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74LVQ04.pdf	22-Dec-99 00:01	63K
74LVQ08.pdf	22-Dec-99 00:01	63K
74LVQ125.pdf	22-Dec-99 00:01	66K
74LVQ138.pdf	22-Dec-99 00:01	98K
74LVQ14.pdf	22-Dec-99 00:01	66K
74LVQ151.pdf	22-Dec-99 00:01	85K
74LVQ157.pdf	22-Dec-99 00:01	79K
74LVQ174.pdf	22-Dec-99 00:01	81K
74LVQ240.pdf	22-Dec-99 00:01	88K
74LVQ241.pdf	22-Dec-99 00:01	88K
74LVQ244.pdf	22-Dec-99 00:01	88K
74LVQ245.pdf	22-Dec-99 00:01	94K
74LVQ273.pdf	22-Dec-99 00:01	89K
74LVQ32.pdf	22-Dec-99 00:01	64K

74LVQ373.pdf	22-Dec-99 00:01	102K
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74LVQ573.pdf	22-Dec-99 00:01	101K
74LVQ74.pdf	22-Dec-99 00:01	86K
74LVQ86.pdf	22-Dec-99 00:01	64K
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74LVT162240.pdf	22-Dec-99 00:01	53K
74LVT162244.pdf	22-Dec-99 00:01	51K
74LVT162245.pdf	22-Dec-99 00:01	78K
74LVT16240.pdf	22-Dec-99 00:01	53K
74LVT16244.pdf	22-Dec-99 00:01	50K
74LVT16244A.pdf	23-Jan-99 00:00	54K
74LVT16245.pdf	22-Dec-99 00:01	76K
74LVT16245A.pdf	12-Feb-99 00:00	55K
74LVT16373.pdf	22-Dec-99 00:01	59K
74LVT16374.pdf	22-Dec-99 00:01	58K
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74LVT16543.pdf	25-Aug-97 15:04	105K
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74LVT2244.pdf	22-Dec-99 00:01	76K
74LVT2245.pdf	10-Jan-00 17:01	93K
74LVT240.pdf	22-Dec-99 00:01	83K
74LVT244.pdf	22-Dec-99 00:01	84K
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74LVT373.pdf	22-Dec-99 00:01	67K

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74LVXC4245.pdf	22-Dec-99 00:01	70K
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74VHC123A.pdf	22-Dec-99 00:01	107K
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74VHC132.pdf	22-Dec-99 00:01	77K
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74VHC14.pdf	22-Dec-99 00:01	75K
74VHC153.pdf	22-Dec-99 00:01	70K
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74VHC161284.pdf	30-Dec-99 00:00	116K
74VHC163.pdf	22-Dec-99 00:01	88K
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74VHC175.pdf	22-Dec-99 00:01	71K
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74VHC595.pdf	22-Dec-99 00:01	83K
74VHC74.pdf	22-Dec-99 00:01	80K
74VHC86.pdf	22-Dec-99 00:01	75K
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74VHCT541A.pdf	22-Dec-99 00:01	83K
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FAIRCHILD SEMICONDUCTOR™

March 1994
Revised November 1999

74ABT125
Quad Buffer with 3-STATE Outputs

General Description

The ABT125 contains four independent non-inverting buffers with 3-STATE outputs.

Features

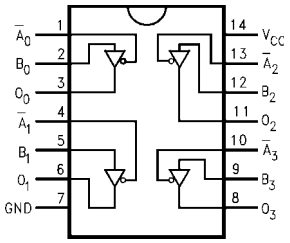
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT125CSC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ABT125CSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT125CMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153,4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Descriptions
$\overline{A}_n$, B_n	Inputs
O_n	Outputs

Function Table

Inputs		Output
A_n	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disabled or Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current (Across Comm Operating Range)	−300 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage					V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test					V	0.0	I_{ID} = 1.9 μA, All Other Pin Grounded
I_{OZH}	Output Leakage Current				10	μA	0–5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0–5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current				−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				15	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC} /Input	Outputs Enabled			1.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			1.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.1	mA/MHz	Max	Outputs Open; $\overline{OE}_n$ = GND, (Note 4); One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

AC Electrical Characteristics

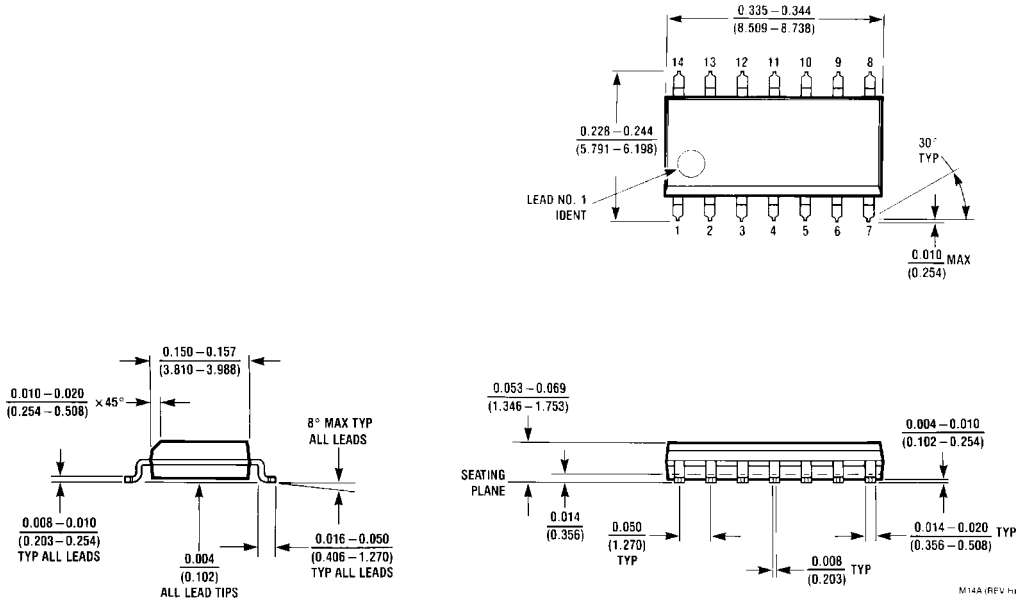
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0		4.6	1.0	4.6	ns
t_{PHL}	Data to Outputs	1.0		4.9	1.0	4.9	
t_{PZH}	Output Enable	1.0		5.1	1.0	5.1	ns
t_{PZL}	Time	1.0		6.8	1.0	6.8	
t_{PHZ}	Output Disable	1.0		6.2	1.0	6.2	ns
t_{PLZ}	Time	1.0		5.5	1.0	5.5	

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

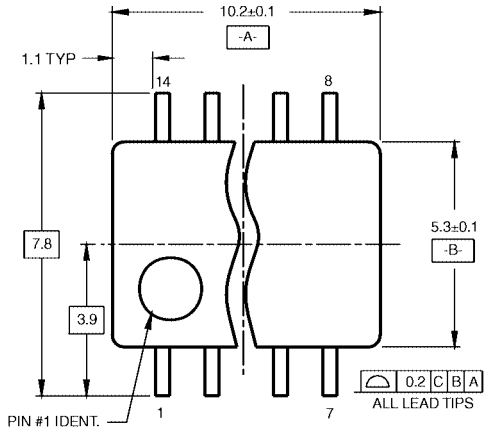
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

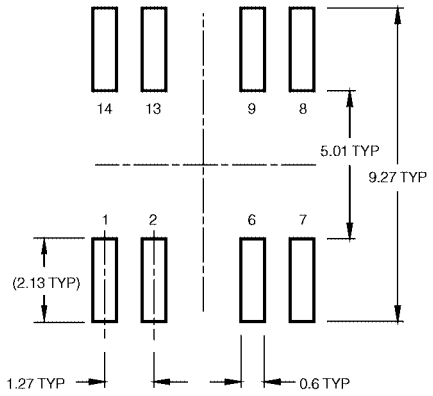
Physical Dimensions inches (millimeters) unless otherwise noted



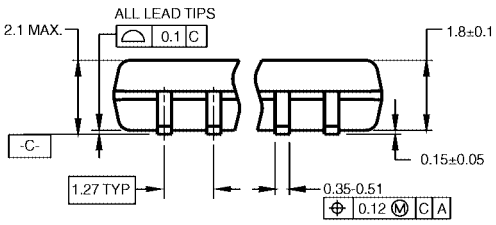
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M14A

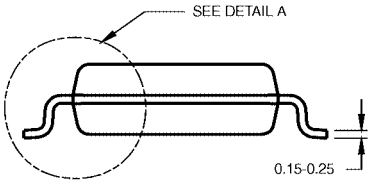
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



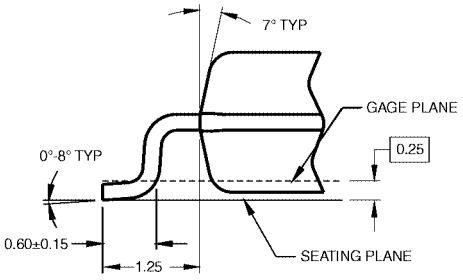


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

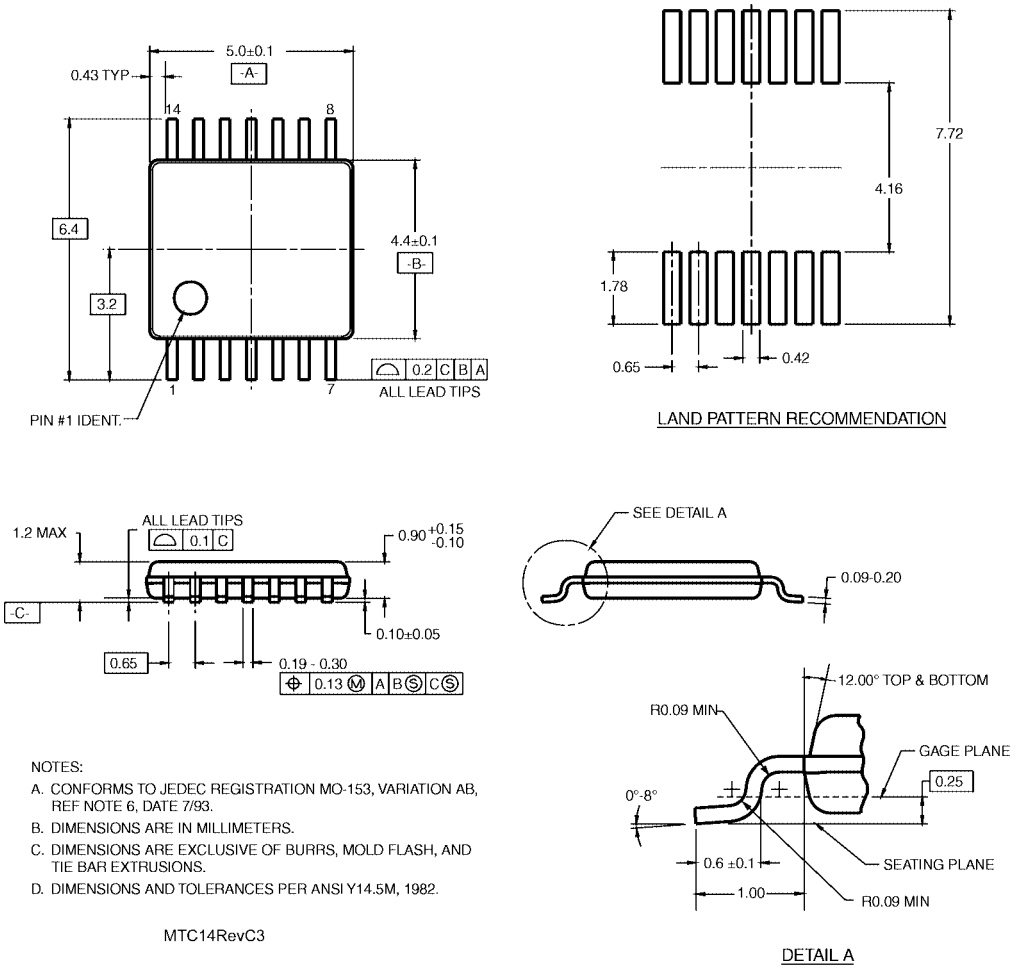
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1995
Revised November 1999

74ABT126
Quad Buffer with 3-STATE Outputs

General Description

The ABT126 contains four independent non-inverting buffers with 3-STATE outputs.

Features

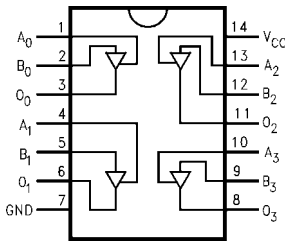
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 m
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT126CSC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ABT126CSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT126CMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Descriptions
A_n, B_n	Inputs
O_n	Outputs

Function Table

Inputs		Output
A_n	B_n	O_n
H	L	L
H	H	H
L	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	
(Across Comm Operating Range)	−300 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	100 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA, All Other Pin Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		-100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				15	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC};
								All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			1.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			1.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC}	No Load				mA/		Outputs Open
	(Note 3)				0.1	MHz	Max	$\overline{OE}_n$ = GND, (Note 4)
								One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

AC Electrical Characteristics

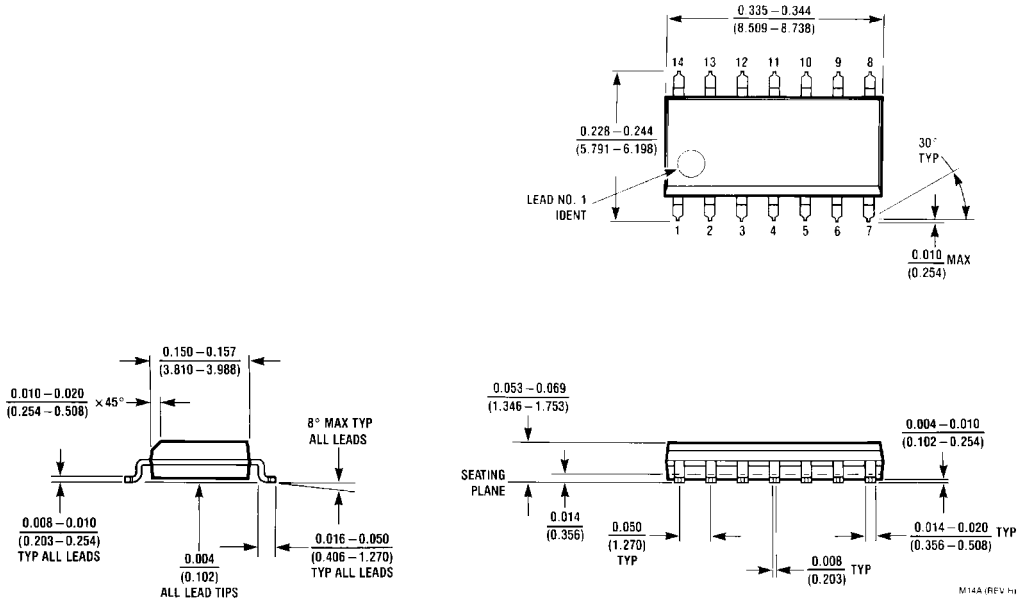
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0		4.4	1.0	4.4	ns
t_{PHL}	Data to Outputs	1.0		4.6	1.0	4.6	
t_{PZH}	Output Enable	1.0		6.5	1.0	6.5	ns
t_{PZL}	Time	1.0		6.5	1.0	6.5	
t_{PHZ}	Output Disable	1.0		5.8	1.0	5.8	ns
t_{PLZ}	Time	1.0		5.5	1.0	5.5	

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

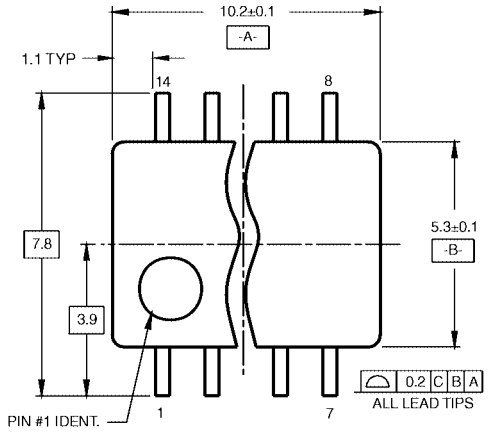
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

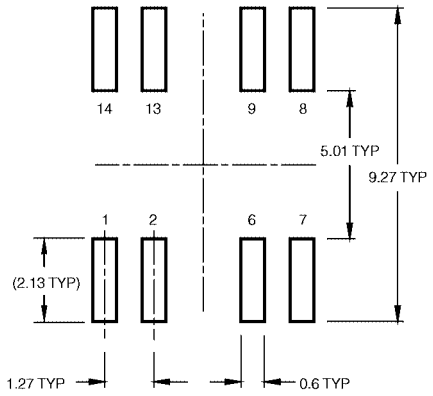
Physical Dimensions inches (millimeters) unless otherwise noted



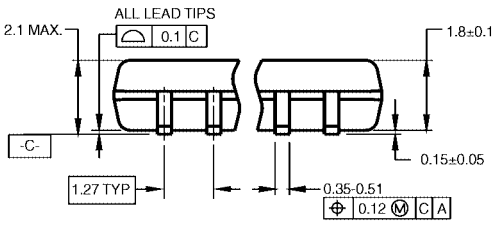
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

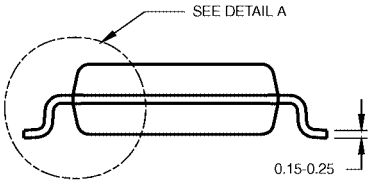
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



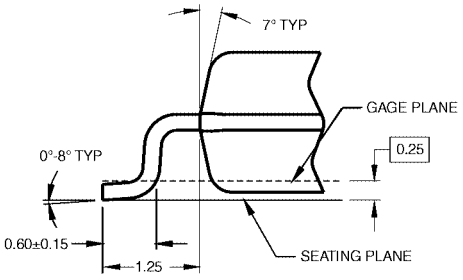


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

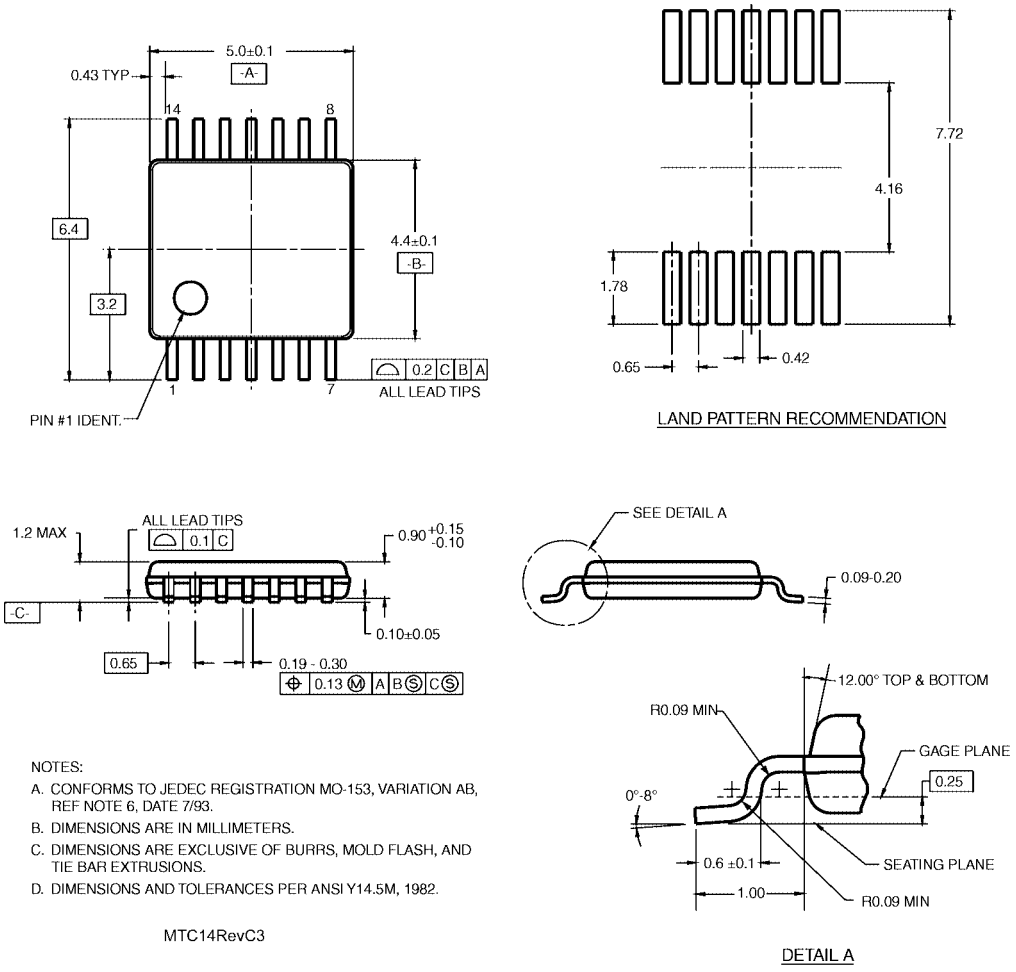
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1992
Revised November 1999

74ABT162244
16-Bit Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The ABT162244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

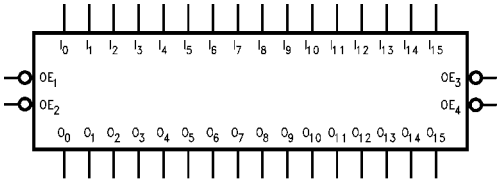
- Separate control logic for each nibble
- 16-bit version of the ABT2244
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

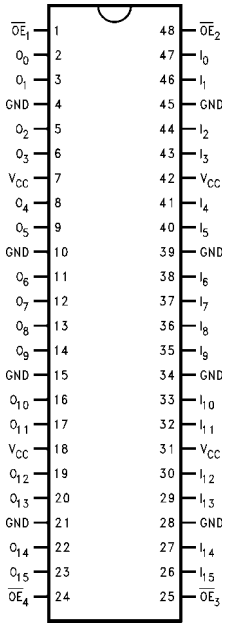
Order Number	Package Number	Package Description
74ABT162244CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT162244CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

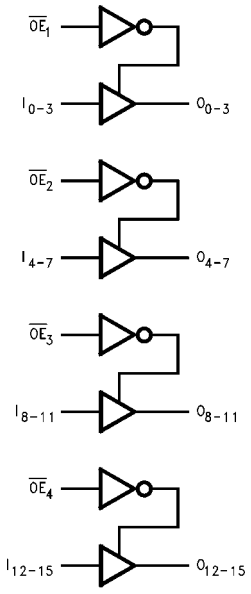
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

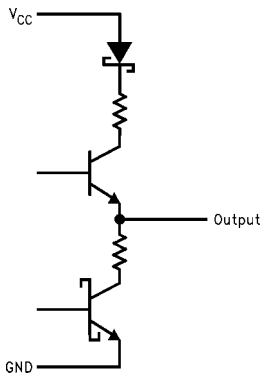
Functional Description

The ABT162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagram



Schematic of each Output



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.8	V	Min	I_{OL} = 12 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				2.0	mA	Max	$\overline{OE}_n$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			3.0	mA		V_I = V_{CC} − 2.1V
		Outputs 3-STATE			3.0	mA	Max	Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.1	mA/MHz	Max	Outputs OPEN $\overline{OE}_n$ = GND One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

AC Electrical Characteristics

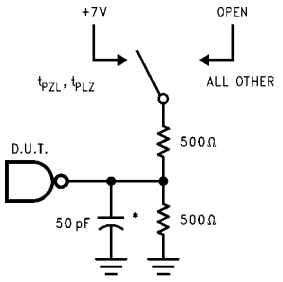
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	1.0	2.4	3.9	1.0	3.9	ns
t_{PHL}	Delay Data to Outputs	1.0	3.2	4.7	1.0	4.7	
t_{PZH}	Output	1.5	3.5	6.3	1.5	6.3	ns
t_{PZL}	Enable Time	1.5	4.2	6.9	1.5	6.9	
t_{PHZ}	Output	1.0	4.2	6.7	1.0	6.7	ns
t_{PLZ}	Disable Time	1.0	3.8	6.7	1.0	6.7	

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0.0V$
C_{OUT} (Note 4)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 4: C_{OUT} is measured at frequency f = 1 MHz per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

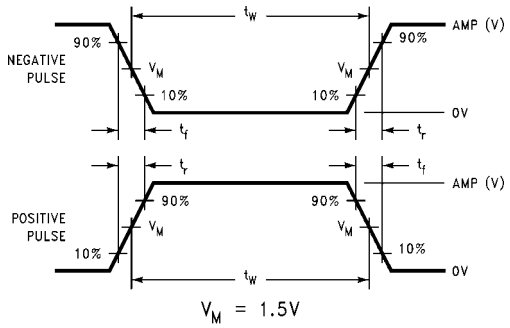


FIGURE 2. Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

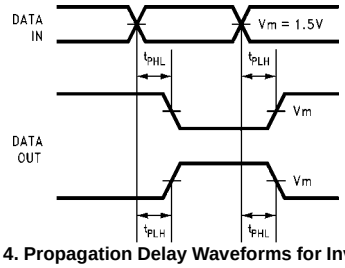


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

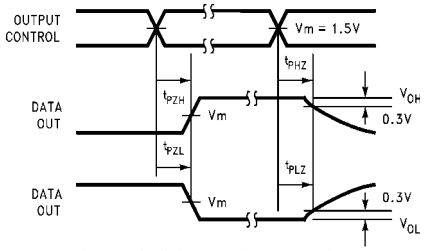


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

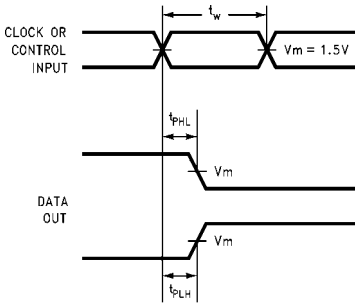


FIGURE 5. Propagation Delay, Pulse Width Waveforms

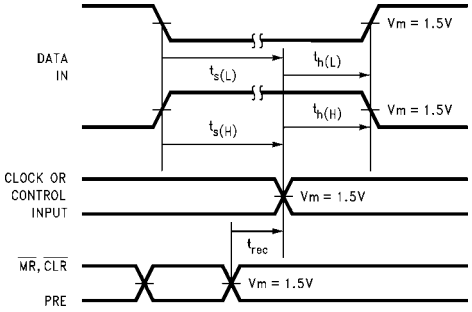
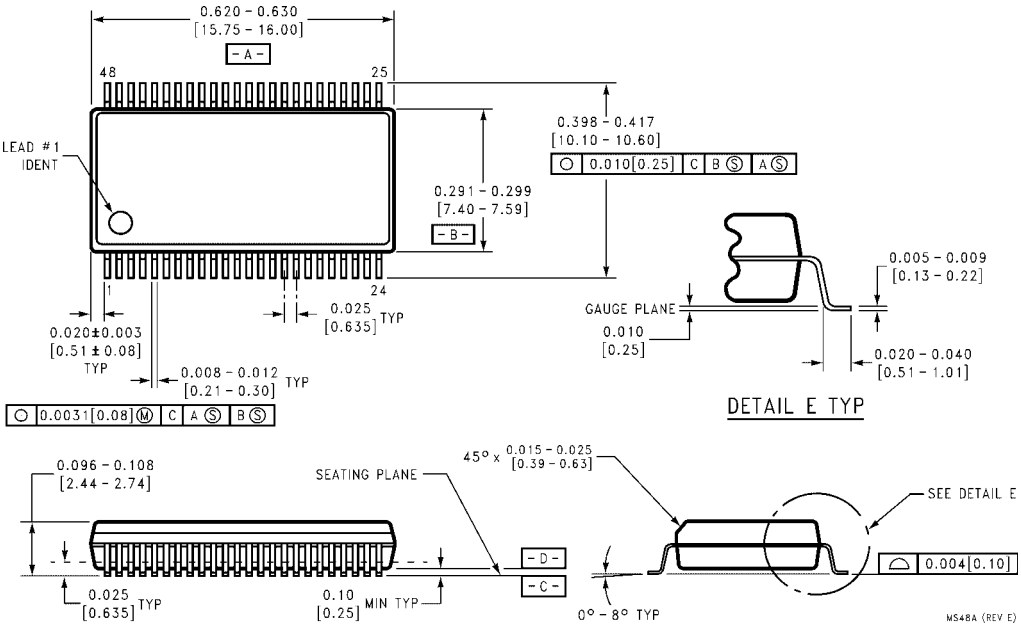


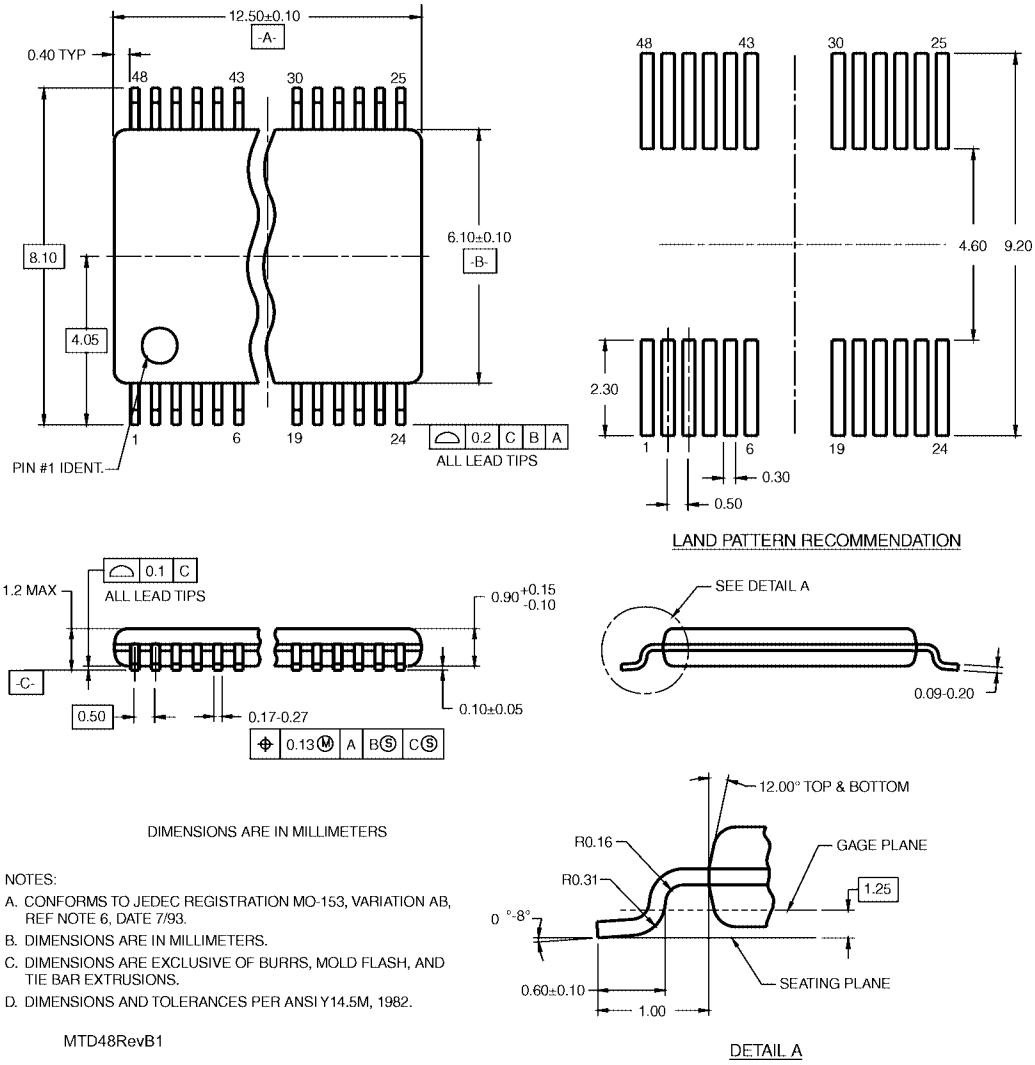
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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April 1992
Revised November 1999

74ABT16244
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT16244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

Features

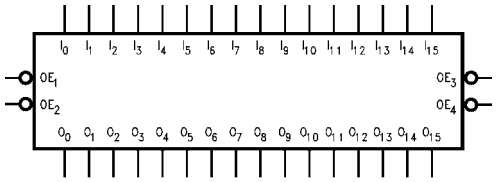
- Separate control logic for each nibble
- 16-bit version of the ABT244
- Outputs sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

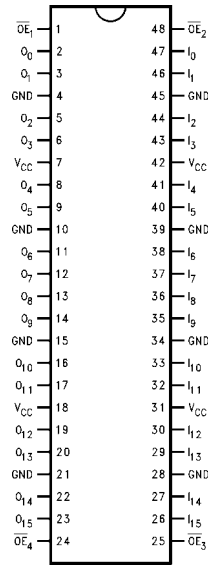
Order Number	Package Number	Package Description
74ABT16244CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16244CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices are also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

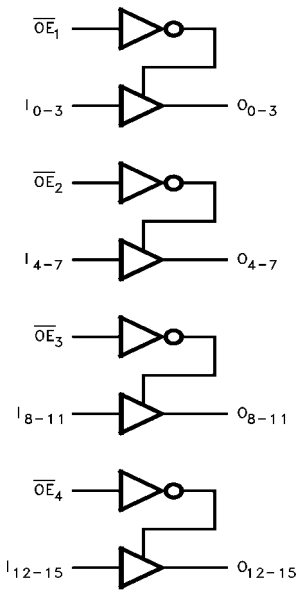
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The ABT16244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V All Other Pins GND
I_{CCH}	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				2.0	mA	Max	$\overline{OE}_n$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA		V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA	Max	Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.1	mA/ MHz	Max	Outputs Open, $\overline{OE}_n$ = GND One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed but not tested.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.4	0.7	V	5.0	T_A = 25°C (Note 4)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.3	–1.0		V	5.0	T_A = 25°C (Note 4)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.0		V	5.0	T_A = 25°C (Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.4		V	5.0	T_A = 25°C (Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 6)

Note 4: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 6: Max number of data inputs (n) switching. n-1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	T_A=+25°C, V_{CC}=+5V, C_L = 50 pF			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	1.0	2.3	3.9	1.0	3.9	ns
t_{PHL}	Delay Data to Outputs	1.0	2.7	3.9	1.0	3.9	
t_{PZH}	Output Enable	1.5	3.5	6.3	1.5	6.3	ns
t_{PZL}	Time	1.5	3.5	6.3	1.5	6.3	
t_{PHZ}	Output Disable	1.0	4.2	6.7	1.0	6.7	ns
t_{PLZ}	Time	1.0	3.2	6.7	1.0	6.7	

Extended AC Electrical Characteristics

Symbol	Parameter	–40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 16 Outputs Switching (Note 7)			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 8)		T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 16 Outputs Switching (Note 9)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.0	ns
t_{PHL}	Data to Outputs	1.5		5.3	1.5	6.0	2.5	8.0	
t_{PZH}	Output Enable Time	1.5		6.5	2.5	7.8	2.5	9.5	ns
t_{PZL}		1.5		6.5	2.5	7.8	2.5	8.5	
t_{PHZ}	Output Disable Time	1.0		6.7	(Note 10)		(Note 10)		ns
t_{PLZ}		1.0		6.7					

Note 7: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 8: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 9: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 10: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 16 Outputs Switching (Note 11) Max	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 16 Outputs Switching (Note 12) Max	Units
t_{OSHL} (Note 13)	Pin to Pin Skew HL Transitions	1.0	1.5	ns
t_{OSLH} (Note 13)	Pin to Pin Skew LH Transitions	1.0	1.5	ns
t_{PS} (Note 14)	Duty Cycle LH–HL Skew	1.5	1.5	ns
t_{OST} (Note 13)	Pin to Pin Skew LH/HL Transitions	1.7	2.0	ns
t_{PV} (Note 15)	Device to Device Skew LH/HL Transitions	2.0	2.5	ns

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 12: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 14: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

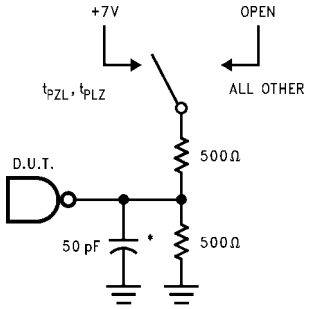
Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 5.0V$
C_{OUT} (Note 16)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 16: C_{OUT} is measured at frequency f = 1 MHz; per MIL STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

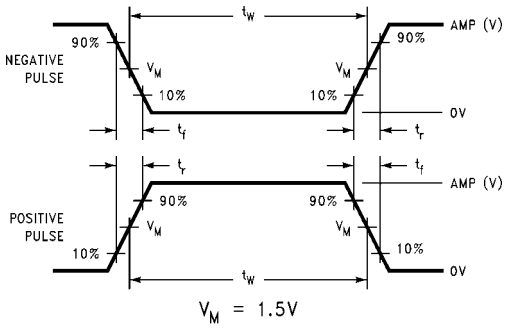


FIGURE 2. Test Input Pulse Requirements

Amplitude	Rep Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

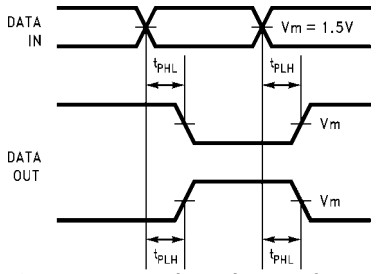


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

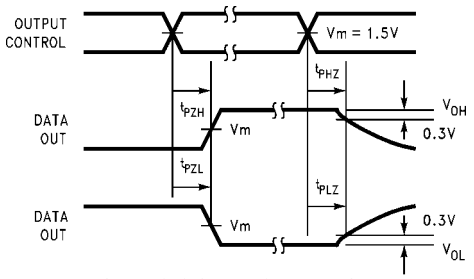


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

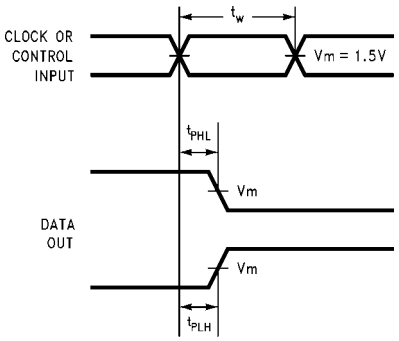


FIGURE 5. Propagation Delay, Pulse Width Waveforms

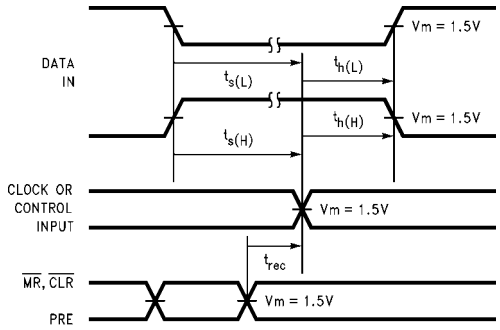
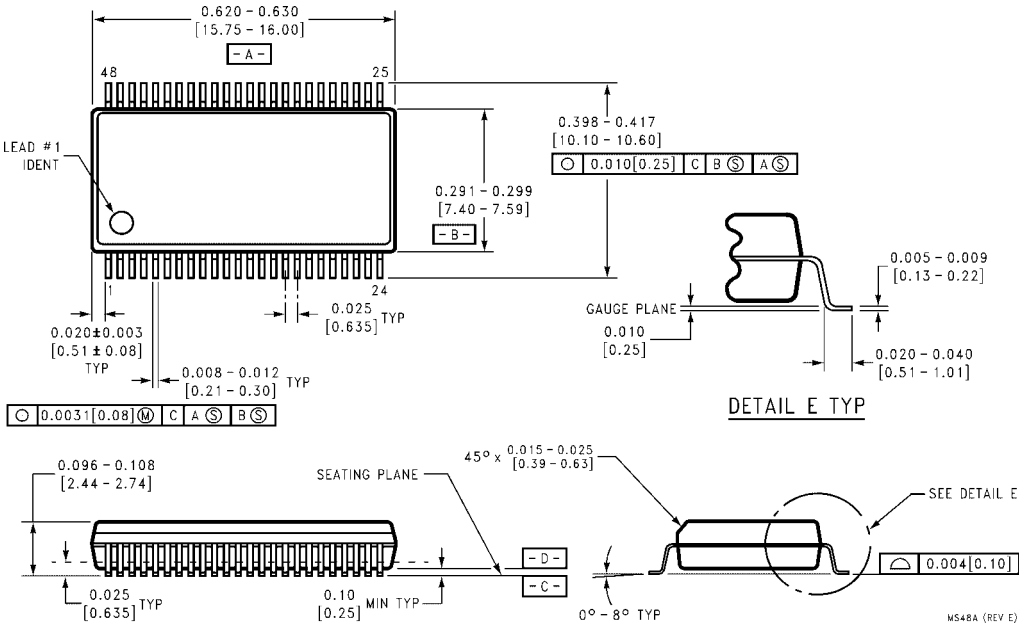


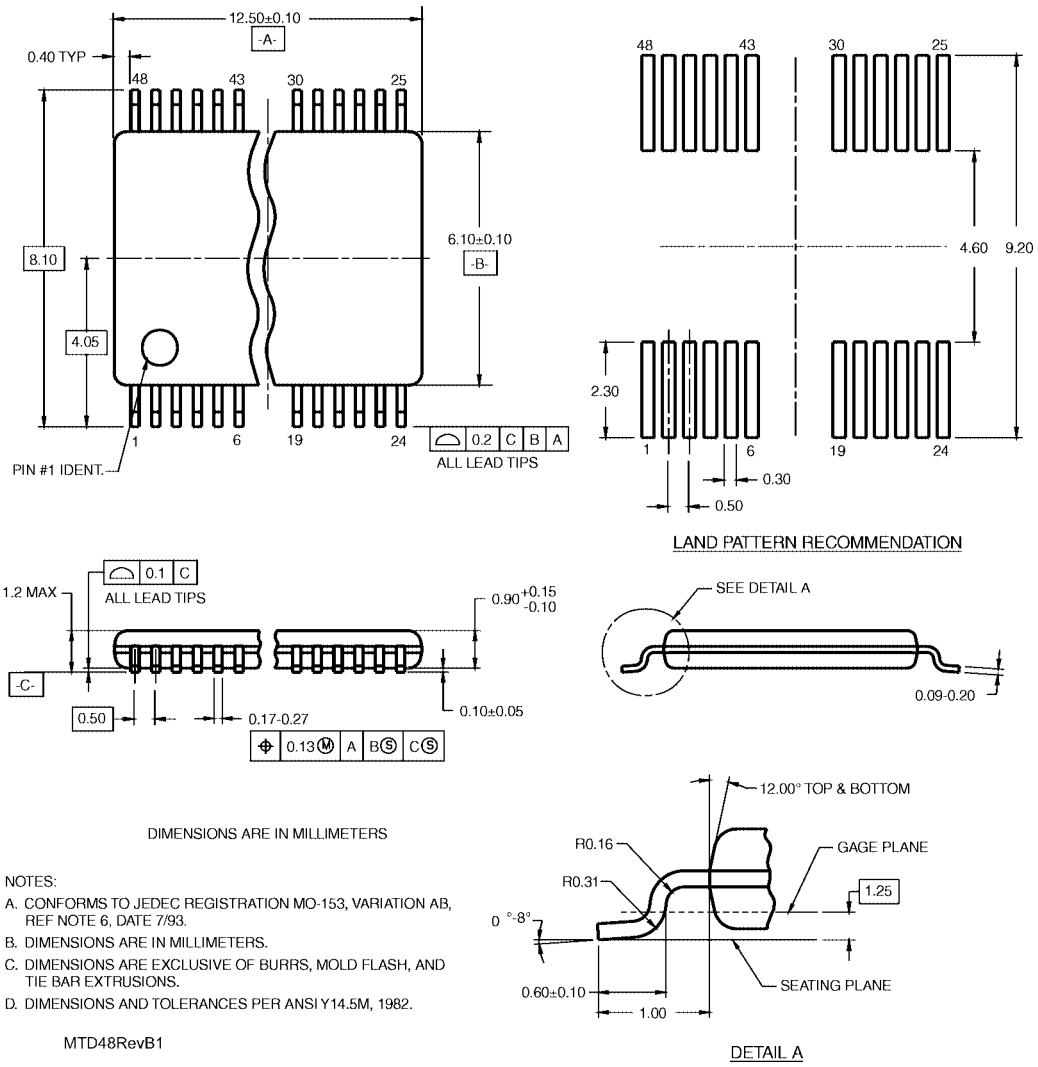
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1992
Revised November 1999

74ABT16245
16-Bit Transceiver with 3-STATE Outputs

General Description

The ABT16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

Features

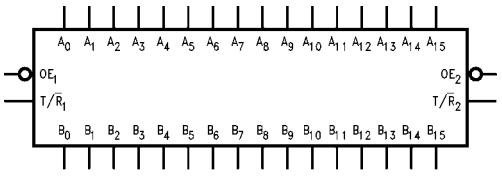
- Bidirectional non-inverting buffers
- Separate control logic for each byte
- 16-bit version of the ABT245
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT16245CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16245CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

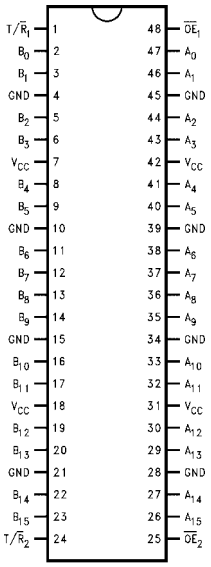
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
T/$\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs/Outputs
B_0–B_{15}	Side B Inputs/Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH-Z State on A_0–A_7, B_0–B_7

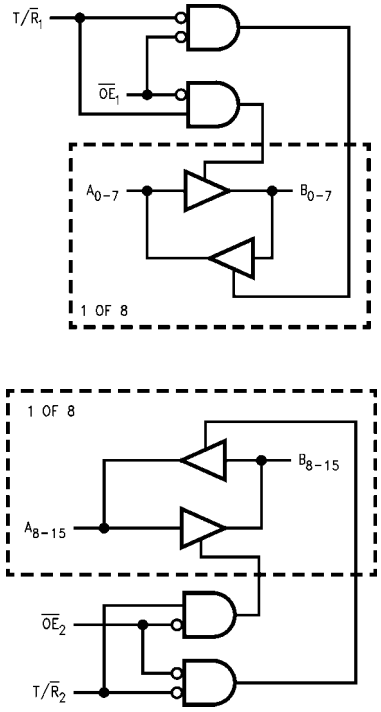
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH-Z State on A_8–A_{15}, B_8–B_{15}

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The ABT16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA ($\overline{OE}_n$, T/$\overline{R}_n$)
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA (A_n, B_n)
			2.0			V	Min	I_{OH} = −32 mA (A_n, B_n)
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V ($\overline{OE}_n$, T/$\overline{R}_n$) (Note 3)
					1			V_{IN} = V_{CC} ($\overline{OE}_n$, T/$\overline{R}_n$)
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V ($\overline{OE}_n$, T/$\overline{R}_n$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)				100	μA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V ($\overline{OE}_n$, T/$\overline{R}_n$) (Note 3)
					−1			V_{IN} = 0.0V ($\overline{OE}_n$, T/$\overline{R}_n$)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA ($\overline{OE}_n$, T/$\overline{R}_n$) All Other Pins Grounded
I_{IH} + I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OE}$ = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.50V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current				100	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				100	μA	Max	$\overline{OE}_n$ = V_{CC}, T/$\overline{R}_n$ = GND or V_{CC} All others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		$\overline{OE}_n$, T/$\overline{R}_n$ V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V All others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.1	mA/MHz	Max	Outputs OPEN $\overline{OE}_n$ = GND, T/$\overline{R}_n$ = GND or V_{CC} One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

DC Extended Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF; R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.5	0.9	V	5.0	T_A = 25°C (Note 4)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.4	–1.0		V	5.0	T_A = 25°C (Note 4)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.4		V	5.0	T_A = 25°C (Note 5)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 6)

Note 4: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 6: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = –55°C to +125°C, V_{CC} = 4.5V – 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V – 5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation	1.0	2.4	3.9	0.5	4.5	1.0	3.9	ns
t_{PHL}	Delay Data to Outputs	1.0	2.8	3.9	0.5	5.2	1.0	3.9	
t_{PZH}	Output Enable	1.5	3.6	6.3	0.8	6.4	1.5	6.3	ns
t_{PZL}	Time	1.5	3.7	6.3	0.9	6.9	1.5	6.3	
t_{PHZ}	Output Disable	1.3	4.6	6.9	1.3	6.9	1.3	6.9	ns
t_{PLZ}	Time	1.3	3.7	6.9	1.0	6.9	1.3	6.9	

Extended AC Electrical Characteristics

Symbol	Parameter	T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 16 Outputs Switching (Note 7)			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 8)		T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 16 Outputs Switching (Note 9)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Maximum Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.0	ns
t_{PHL}	Data to Outputs	1.5		5.3	1.5	6.0	2.5	8.0	
t_{PZH}	Output Enable	1.5		6.5	2.5	8.2	2.5	10.0	ns
t_{PZL}	Time	1.5		6.5	2.5	8.2	2.5	9.0	
t_{PHZ}	Output Disable	1.0		6.9	(Note 10)		(Note 10)		ns
t_{PLZ}	Time	1.0		6.9					

Note 7: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 8: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 9: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 10: 3-STATE delay are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 16 Outputs Switching (Note 11)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 16 Outputs Switching (Note 12)	Units
		Max	Max	
t_{OSHL} (Note 13)	Pin to Pin Skew HL Transitions	1.3	1.5	ns
t_{OSLH} (Note 13)	Pin to Pin Skew LH Transitions	1.3	1.5	ns
t_{PS} (Note 14)	Duty Cycle LH–HL Skew	1.5	2.0	ns
t_{OST} (Note 13)	Pin to Pin Skew LH/HL Transitions	1.7	2.5	ns
t_{PV} (Note 15)	Device to Device Skew LH/HL Transitions	2.0	3.0	ns

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 12: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 14: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

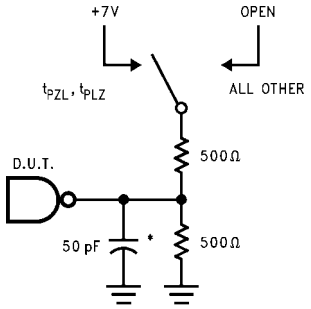
Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0.0V$ ($\overline{OE}_n$, $T/\overline{R}_n$)
$C_{I/O}$ (Note 16)	Output Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 16: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

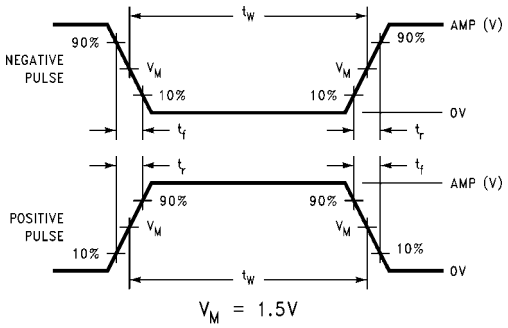


FIGURE 2. Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

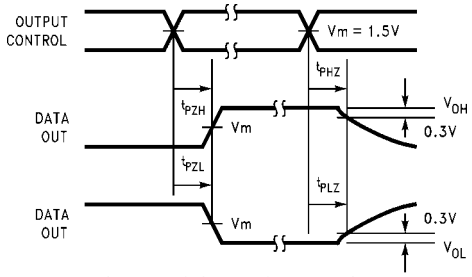


FIGURE 4. 3-STATE Output HIGH and LOW Enable and Disable Times

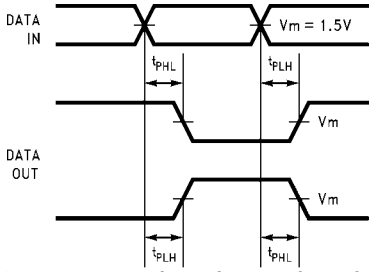


FIGURE 6. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

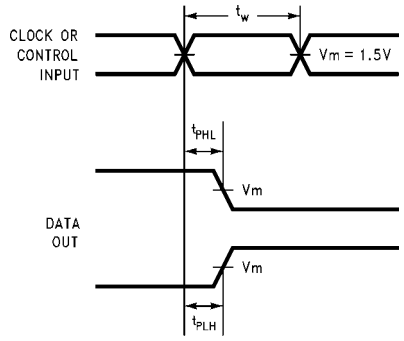


FIGURE 5. Propagation Delay, Pulse Width Waveforms

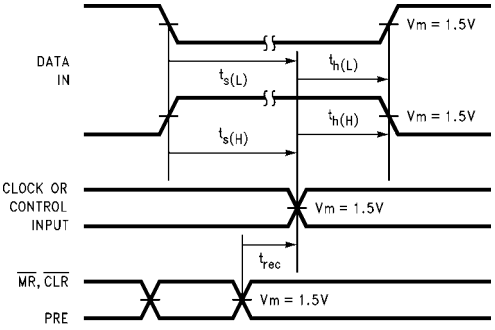
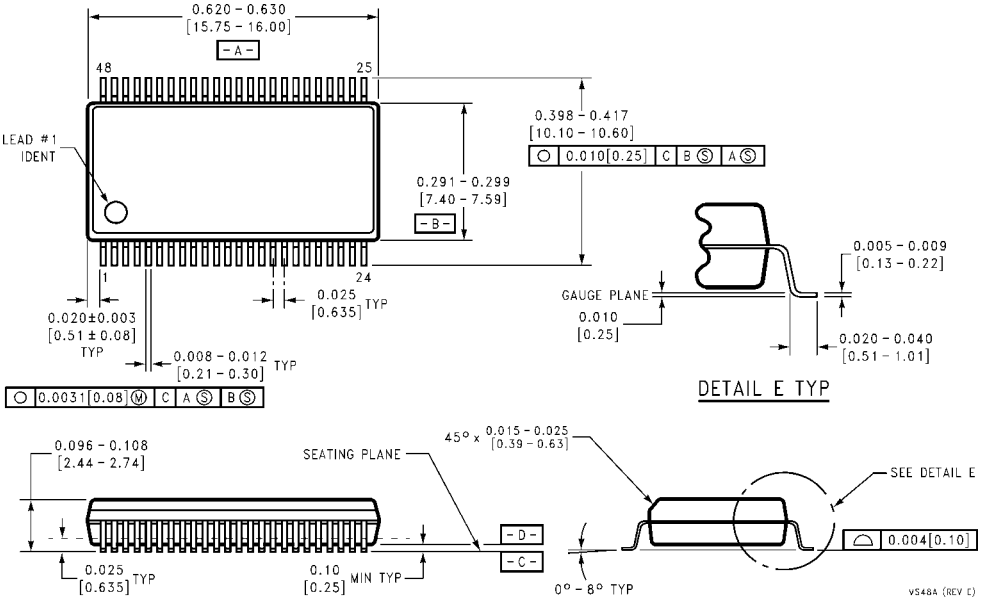


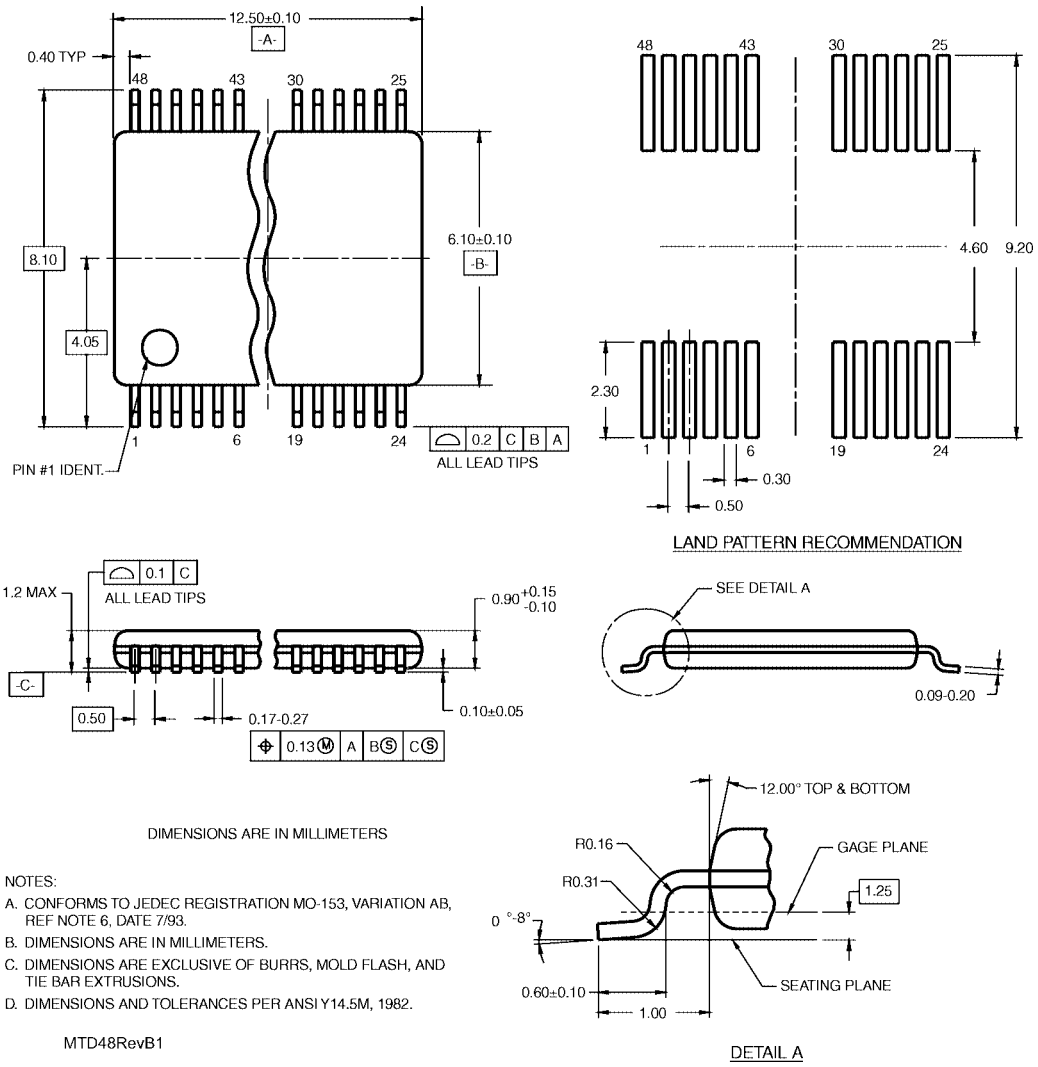
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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March 1994
Revised November 1999

74ABT16373
16-Bit Transparent D-Type Latch with 3-STATE Outputs

General Description

The ABT16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in high Z state.

Features

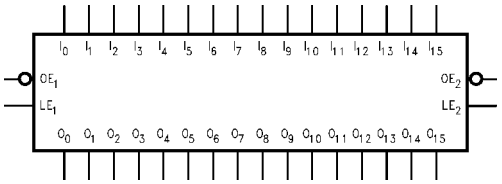
- Separate control logic for each byte
- 16-bit version of the ABT373
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Guaranteed latch-up protection

Ordering Code:

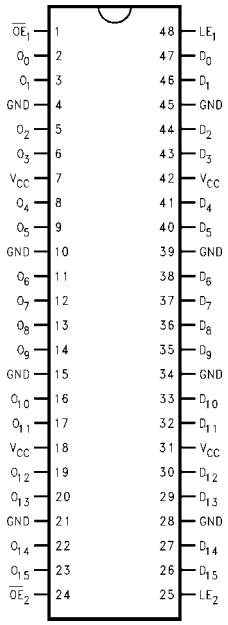
Order Number	Package Number	Package Description
74ABT16373CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16373CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
D_0–D_{15}	Data Inputs
O_0–O_{15}	Outputs

Functional Description

The ABT16373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the D_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change states each time its D input changes. When LE_n is LOW, the latches store information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

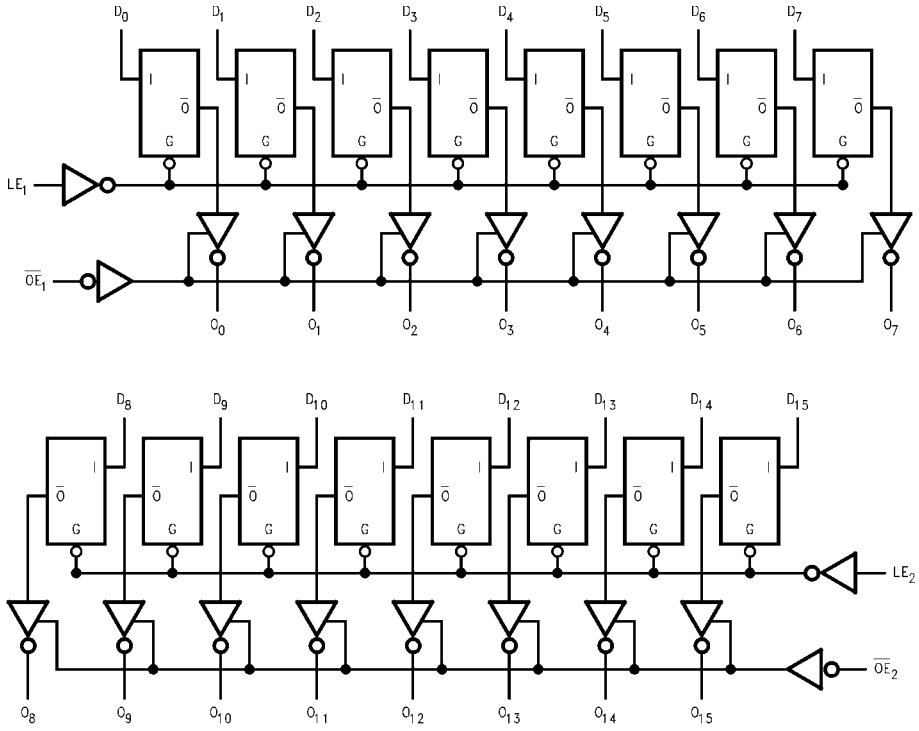
Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	D_0–D_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	(Previous)

Inputs			Outputs
LE_2	$\overline{OE}_2$	D_8–D_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	(Previous)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
Previous = previous output prior to HIGH-to-LOW transition of LE

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current: $\overline{OE}$ Pin	−350 mA
(Across Comm Operating Range)	
Other Pins	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5 2.0				Min	I_{OH} = −3 mA I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1 1	μA	Max	V_{IN} = 2.7V (Note 3) V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1 −1	μA	Max	V_{IN} = 0.5V (Note 3) V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				62	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				2.0	mA	Max	$\overline{OE}$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA		V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA	Max	Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.15	mA/ MHz	Max	Outputs Open, LE = V_{CC} $\overline{OE}$ = GND, (Note 4) One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

AC Electrical Characteristics

(SOIC and SSOP Packages)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.4		5.6	1.4	5.6	ns
t_{PHL}	D_n to O_n	1.4		5.6	1.4	5.6	
t_{PLH}	Propagation Delay	1.7		6.0	1.7	6.0	ns
t_{PHL}	LE to O_n	1.7		5.5	1.7	5.5	
t_{PZH}	Output Enable Time	1.1		6.1	1.1	6.1	ns
t_{PZL}		1.5		5.6	1.5	5.6	
t_{PHZ}	Output Disable Time	2.4		7.1	2.4	7.1	ns
t_{PLZ}		1.6		6.5	1.6	6.5	

AC Operating Requirements

(SOIC and SSOP Packages)

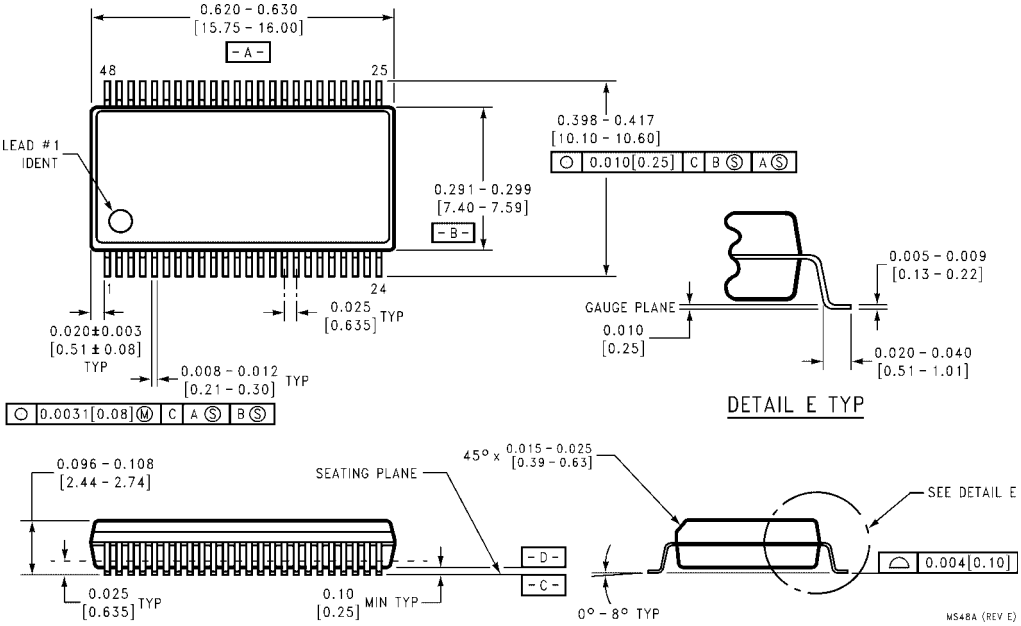
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{TOGGLE}	Maximum Toggle Frequency		100				MHz
$t_S(H)$	Setup Time, HIGH	1.5			1.5		ns
$t_S(L)$	or LOW D_n to LE	1.5			1.5		
$t_H(H)$	Hold Time, HIGH	1.0			1.0		ns
$t_H(L)$	or LOW D_n to LE	1.0			1.0		
$t_W(H)$	Pulse Width, LE HIGH	3.0			3.0		ns

Capacitance

Symbol	Parameter	Typ	Units	Conditions ($T_A = 25°C$)
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	11	pF	$V_{CC} = 5.0V$

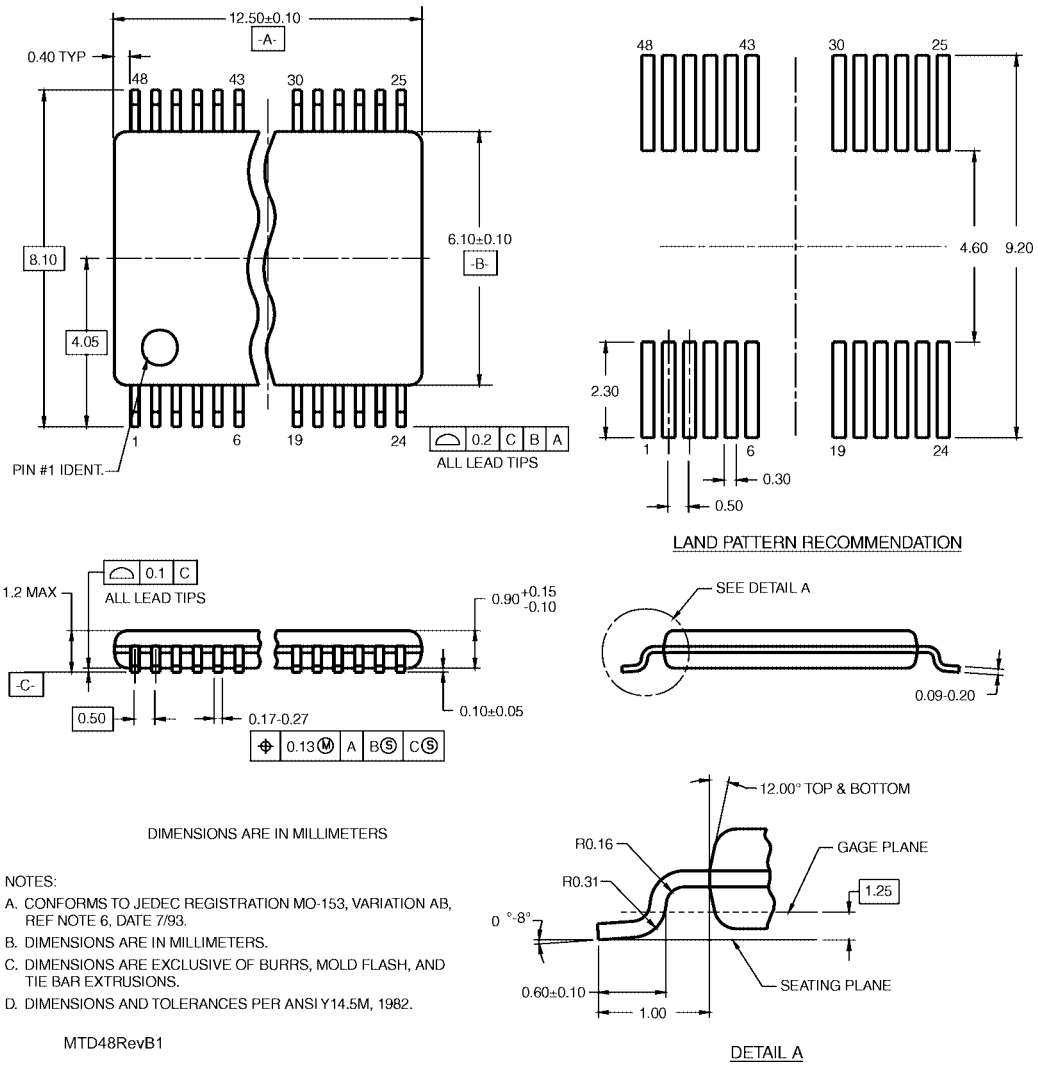
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1994
Revised November 1999

74ABT16374
16-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ABT16374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and Output Enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

Features

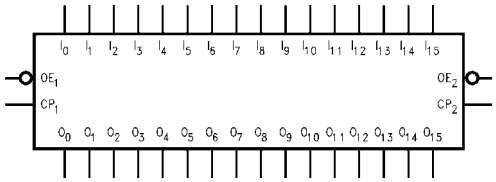
- Separate control logic for each byte
- 16-bit version of the ABT374
- Edge-triggered D-type inputs
- Buffered Positive edge-triggered clock
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Guaranteed latch-up protection

Ordering Code:

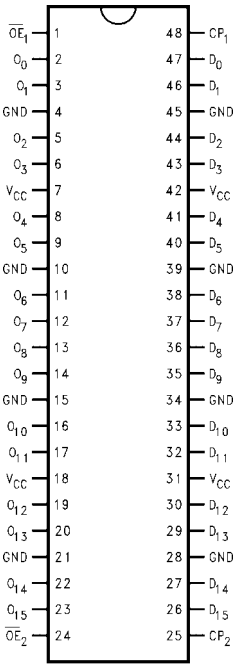
Order Number	Package Number	Package Description
74ABT16374CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16374CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Name	Description
$\overline{OE}_n$	3-STATE Output Enable Input (Active LOW)
CP_n	Clock Pulse Input (Active Rising Edge)
D_0–D_{15}	Data Inputs
O_0–O_{15}	3-STATE Outputs

Functional Description

The ABT16374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each byte has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operation of the OE_n input does not affect the state of the flip-flops.

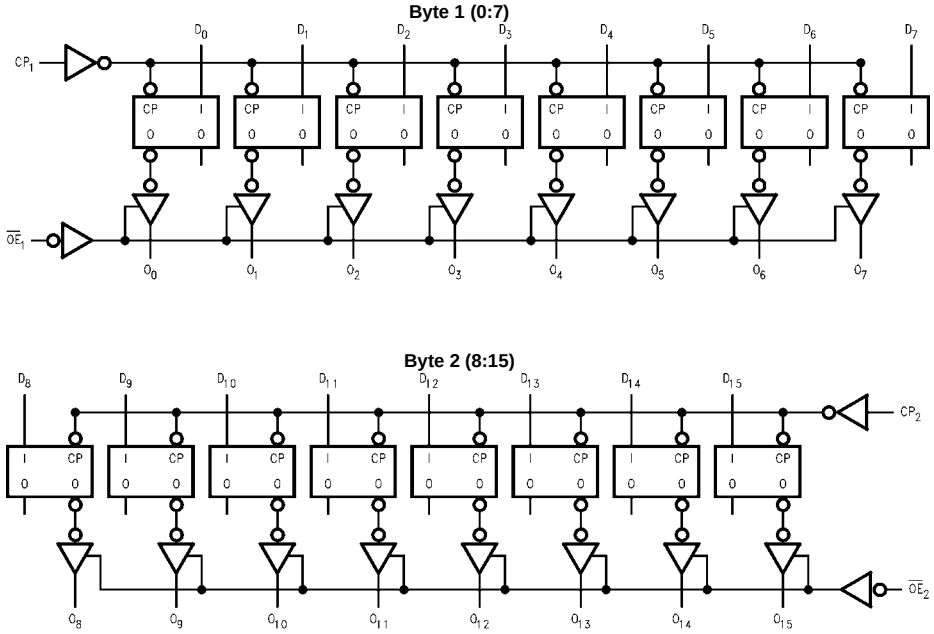
Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	D_0–D_7	O_0–O_7
⌐	L	H	H
⌐	L	L	L
L	L	X	(Previous)
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	D_8–D_{15}	O_8–O_{15}
⌐	L	H	H
⌐	L	L	L
L	L	X	(Previous)
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current:	
$\overline{OE}$ Pin	−350 mA
(Across Comm Operating Range)	
Other Pins	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0–5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0–5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others V_{CC} or GND
I_{CCH}	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				62	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				2.0	mA	Max	$\overline{OE}$ = V_{CC}; All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V All Others at V_{CC}or GND
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.30	mA/MHz	Max	Outputs Open $\overline{OE}$ = GND, (Note 4) One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8-bit toggling, I_{CCD} < 0.8 mA/MHz.

AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150			150		MHz
t_{PLH}	Propagation Delay	1.8		6.2	1.8	6.2	ns
t_{PHL}	CP to O_n	1.8		5.9	1.8	5.9	
t_{PZH}	Output Enable Time	1.2		5.6	1.2	5.6	ns
t_{PZL}		1.6		5.3	1.6	5.3	
t_{PHZ}	Output Disable Time	2.2		7.1	2.2	7.1	ns
t_{PLZ}		2.2		6.6	2.2	6.6	

AC Operating Requirements

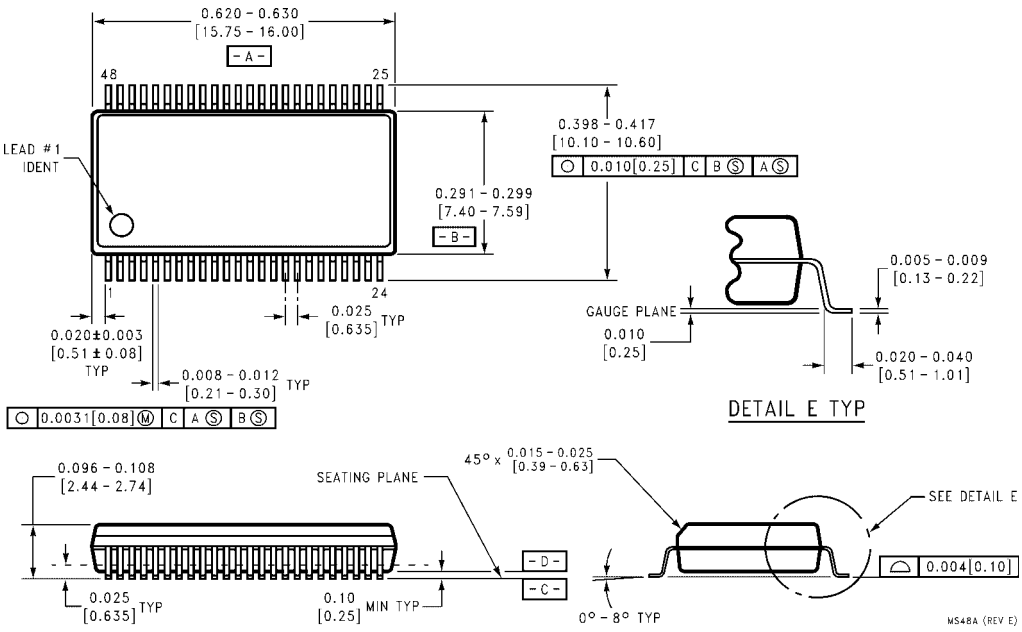
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH	1.1		1.1		ns
$t_S(L)$	or LOW D_n to CP	1.1		1.1		
$t_H(H)$	Hold Time, HIGH	1.3		1.3		ns
$t_H(L)$	or LOW D_n to CP	1.3		1.3		
$t_W(H)$	Pulse Width, CP	3.0		3.0		ns
$t_W(L)$	HIGH or LOW	3.0		3.0		

Capacitance

Symbol	Parameter	Typ	Units	Conditions ($T_A = 25°C$)
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	11.0	pF	$V_{CC} = 5.0V$

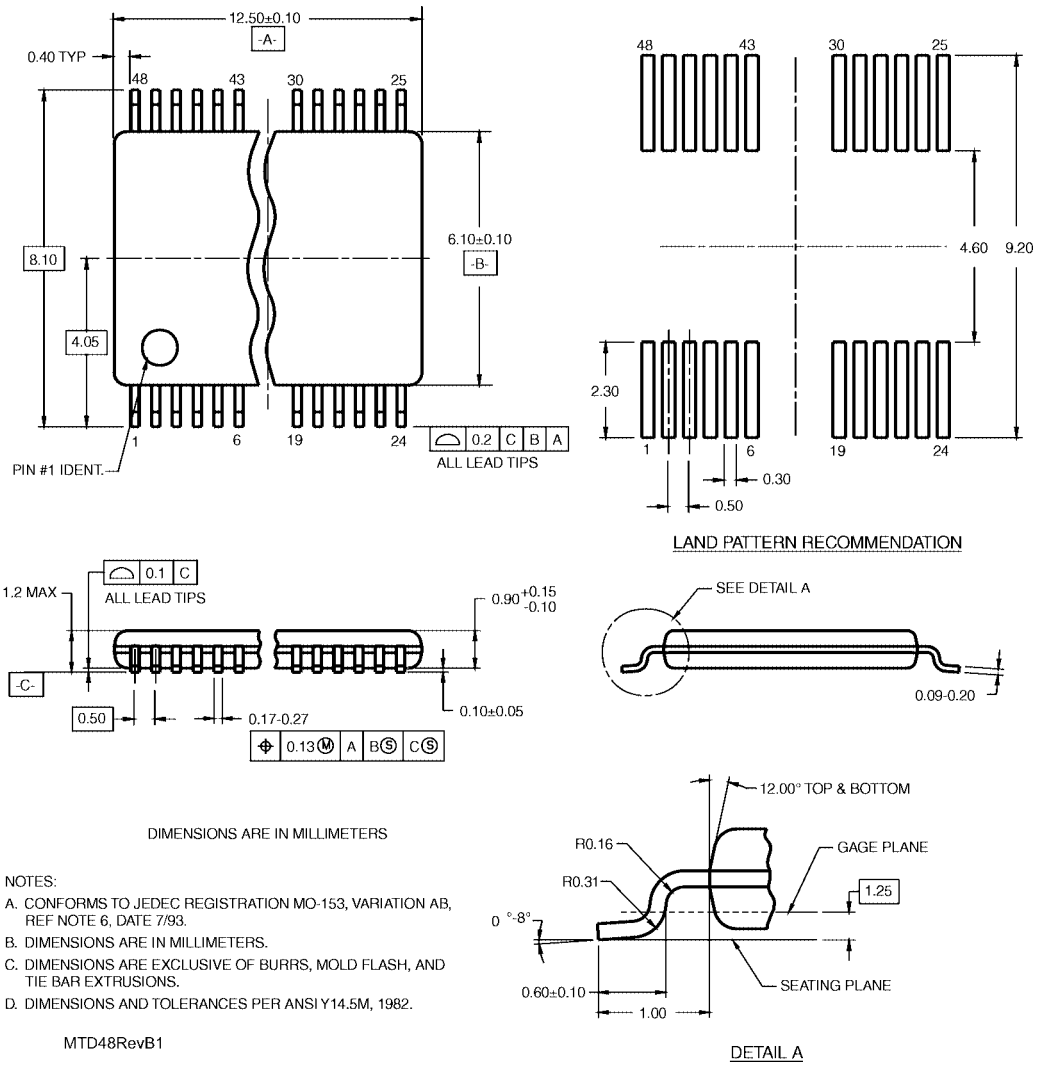
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1993
Revised January 1999

74ABT16500
18-Bit Universal Bus Transceivers with 3-STATE Outputs

General Description

The ABT16500 18-bit universal bus transceiver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and $\overline{\text{OEBA}}$), latch-enable (LEAB and LEBA), and clock ($\overline{\text{CLKAB}}$ and $\overline{\text{CLKBA}}$) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if $\overline{\text{CLKAB}}$ is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the HIGH-to-LOW transition of $\overline{\text{CLKAB}}$. Output-enable OEAB is active-high. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{\text{OEBA}}$, LEBA, and $\overline{\text{CLKBA}}$. The output enables are complementary (OEAB is active HIGH and $\overline{\text{OEBA}}$ is active LOW).

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Features

- Combines D-Type latches and D-Type flip-flops for operation in transparent, latched, or clocked mode
- Flow-through architecture optimizes PCB layout
- Guaranteed latch-up protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

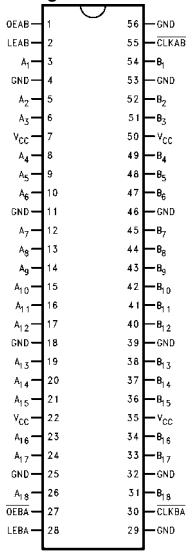
Ordering Code:

Order Number	Package Number	Package Description
74ABT16500CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16500CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the letter suffix "X" to the ordering code.

Connection Diagram

Pin Assignment for SSOP



Function Table (Note 1)

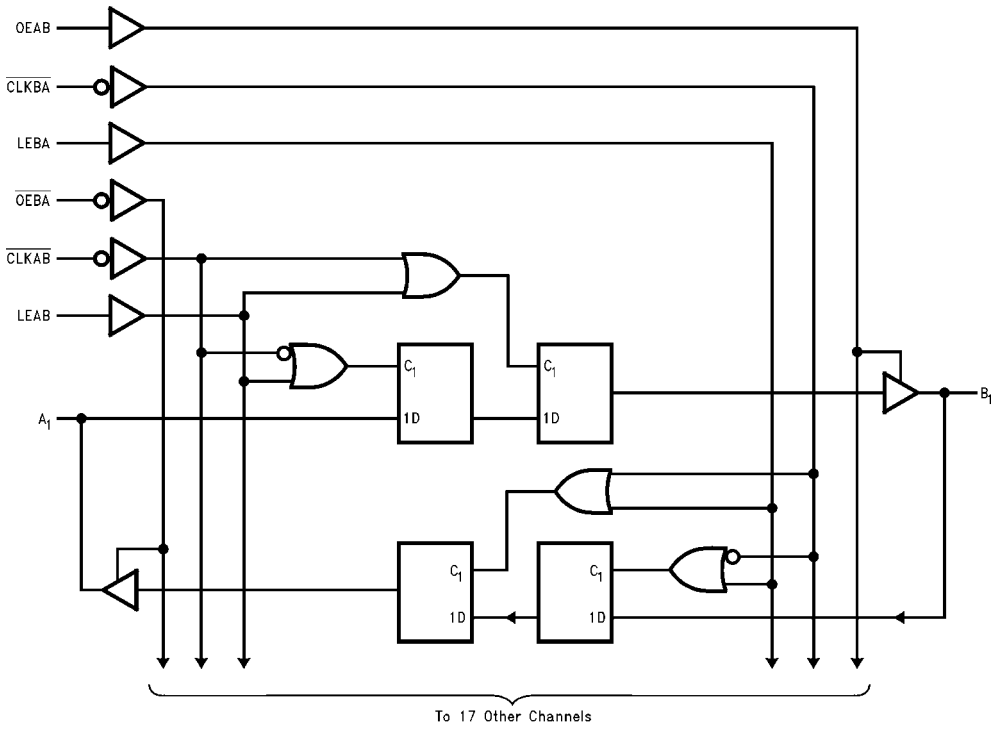
Inputs				Output
OEAB	LEAB	$\overline{\text{CLKAB}}$	A	B
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↓	L	L
H	L	↓	H	H
H	L	H	X	B_0 (Note 2)
H	L	L	X	B_0 (Note 3)

Note 1: A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{\text{OEBA}}$, LEBA, and $\overline{\text{CLKBA}}$.

Note 2: Output level before the indicated steady-state input conditions were established.

Note 3: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CLKAB}}$ was LOW before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings(Note 4)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 5)	−0.5V to +7.0V
Input Current (Note 5)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disabled or Power-off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 4: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 5: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.5			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Note 6)
				1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Note 6)
				−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{IH} + I_{OZH}	Output Leakage Current			10	µA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}$, OE = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current			−10	µA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}$, OE = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			68	µA	Max	An or Bn Outputs Low
I_{CCZ}	Power Supply Current			1.0	mA	Max	$\overline{OE}_n$ = V_{CC}, All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 6)			0.23	mA/MHz	Max	Outputs Open Transparent Mode One Bit Toggling, 50% Duty Cycle

Note 6: Guaranteed, but not tested.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF; R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.2	V	5.0	T_A = 25°C (Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.5	−1.0		V	5.0	T_A = 25°C (Note 7)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 8)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	T_A = 25°C (Note 9)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 9)

Note 7: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 8: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 9: Max number of data inputs (n) switching. n − 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	150	200		150		MHz
t_{PLH}	Propagation Delay	1.5	2.7	4.6	1.5	4.6	ns
t_{PHL}	A or B to B or A	1.5	3.2	4.6	1.5	4.6	
t_{PLH}	Propagation Delay	1.5	3.1	5.0	1.5	5.0	ns
t_{PHL}	LEAB or LEBA to B or A	1.5	3.6	5.0	1.5	5.0	
t_{PLH}	Propagation Delay	1.5	3.4	5.3	1.5	5.3	ns
t_{PHL}	$\overline{CLKAB}$ or $\overline{CLKBA}$ to B or A	1.5	3.7	5.3	1.5	5.3	
t_{PZH}	Propagation Delay	1.5	2.7	5.6	1.5	5.6	ns
t_{PZL}	OEAB or $\overline{OEBA}$ to B or A	1.5	3.0	5.6	1.5	5.6	
t_{PHZ}	Propagation Delay	1.5	3.7	6.0	1.5	6.0	ns
t_{PLZ}	OEAB or $\overline{OEBA}$ to B or A	1.5	3.2	6.0	1.5	6.0	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time,	4.5		4.5		ns
$t_S(L)$	A to $\overline{CLKAB}$	4.5		4.5		
$t_H(H)$	Hold Time,	0		0		ns
$t_H(L)$	A to $\overline{CLKAB}$	0		0		
$t_S(H)$	Setup Time,	4.0		4.0		ns
$t_S(L)$	B to $\overline{CLKBA}$	4.0		4.0		
$t_H(H)$	Hold Time,	0		0		ns
$t_H(L)$	B to $\overline{CLKBA}$	0		0		
$t_S(H)$	Setup Time, A to LEAB	1.5		1.5		ns
$t_S(L)$	or B to LEBA, $\overline{CLK}$ HIGH	1.5		1.5		
$t_H(H)$	Hold Time, A to LEAB	1.5		1.5		ns
$t_H(L)$	or B to LEBA, $\overline{CLK}$ HIGH	1.5		1.5		
$t_S(H)$	Setup Time, A to LEAB	4.5		4.5		ns
$t_S(L)$	or B to LEBA, $\overline{CLK}$ LOW	4.5		4.5		
$t_H(H)$	Hold Time, A to LEAB	1.5		1.5		ns
$t_H(L)$	or B to LEBA, $\overline{CLK}$ LOW	1.5		1.5		
$t_W(H)$	Pulse Width,	3.3		3.3		ns
$t_W(L)$	LEAB or LEBA, HIGH	3.3		3.3		
$t_W(H)$	Pulse Width, $\overline{CLKAB}$	3.3		3.3		ns
$t_W(L)$	or $\overline{CLKBA}$, HIGH or LOW	3.3		3.3		

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 18 Outputs Switching (Note 10)			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 11)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 18 Outputs Switching (Note 12)		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5		6.5	2.0	7.0	2.5	9.9	ns
t_{PHL}	Data to Outputs	1.5		6.5	2.0	7.0	2.5	9.2	
t_{PLH}	Propagation Delay	1.5		6.0	2.0	7.5	2.5	8.5	ns
t_{PHL}	LEAB or LEBA to B or A	1.5		6.0	2.0	7.5	2.5	8.5	
t_{PLH}	Propagation Delay	1.5		6.2	2.0	7.7	2.5	8.5	ns
t_{PHL}	$\overline{CLKAB}$ or $\overline{CLKBA}$ to B or A	1.5		6.2	2.0	7.7	2.5	8.5	
t_{PZH}	Output Enable Time	1.5		6.5	2.0	7.0	2.5	8.5	ns
t_{PZL}		1.5		6.5	2.5	7.0	2.5	8.5	
t_{PHZ}	Output Disable	1.5		6.5	(Note 13)		(Note 13)		ns
t_{PLZ}	Time	1.5		6.5					

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 18 Outputs Switching (Note 14)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 18 Outputs Switching (Note 15)	Units
		Max	Max	
t_{OSHL} (Note 16)	Pin to Pin Skew HL Transitions	2.0	2.8	ns
t_{OSLH} (Note 16)	Pin to Pin Skew LH Transitions	2.0	2.5	ns
t_{PS} (Note 17)	Duty Cycle LH–HL Skew	2.0	2.8	ns
t_{OST} (Note 16)	Pin to Pin Skew LH/HL Transitions	2.5	3.0	ns
t_{PV} (Note 18)	Device to Device Skew LH/HL Transitions	3.0	3.5	ns

Note 14: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 15: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 16: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 17: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

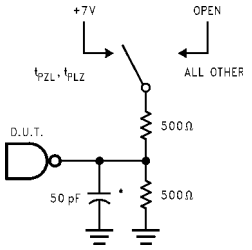
Note 18: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0.0V$
$C_{I/O}$ (Note 19)	Output Capacitance	11.0	pF	$V_{CC} = 5.0V$

Note 19: $C_{I/O}$ is measured at frequency f = 1 MHz per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance.

FIGURE 1. Standard AC Test Load

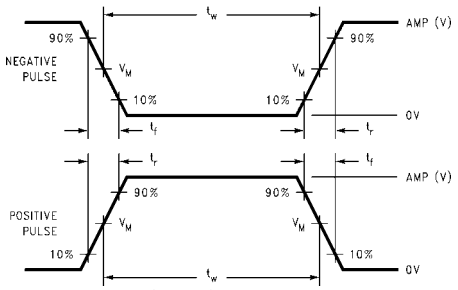


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

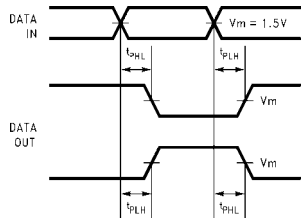


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

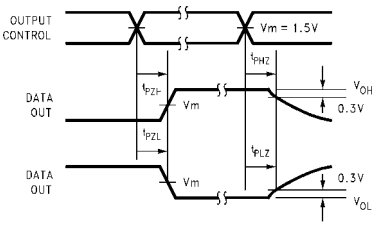


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

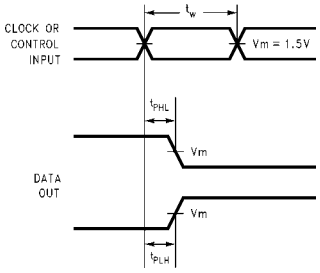


FIGURE 5. Propagation Delay, Pulse Width Waveforms

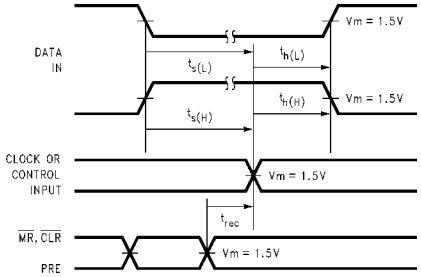
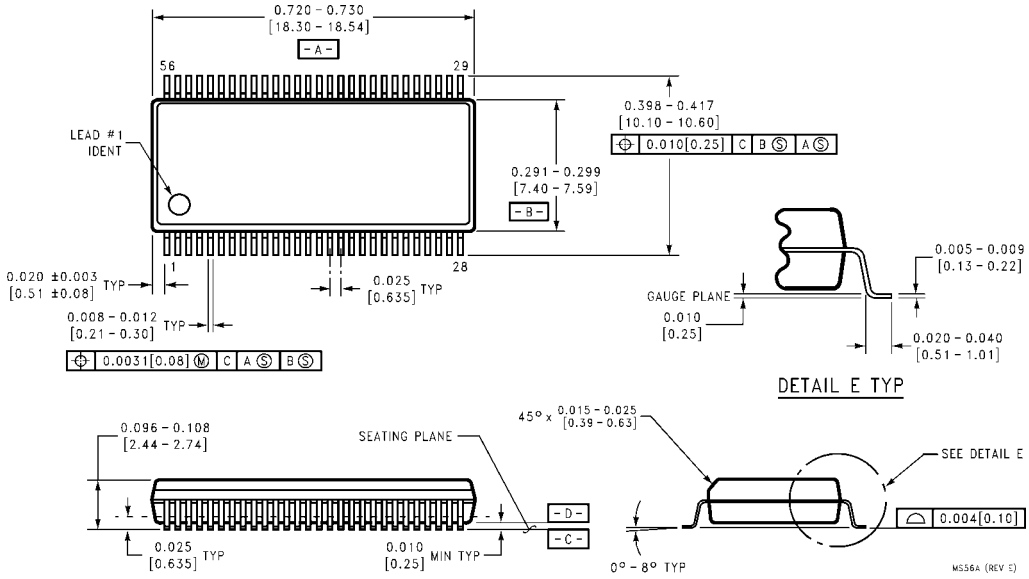


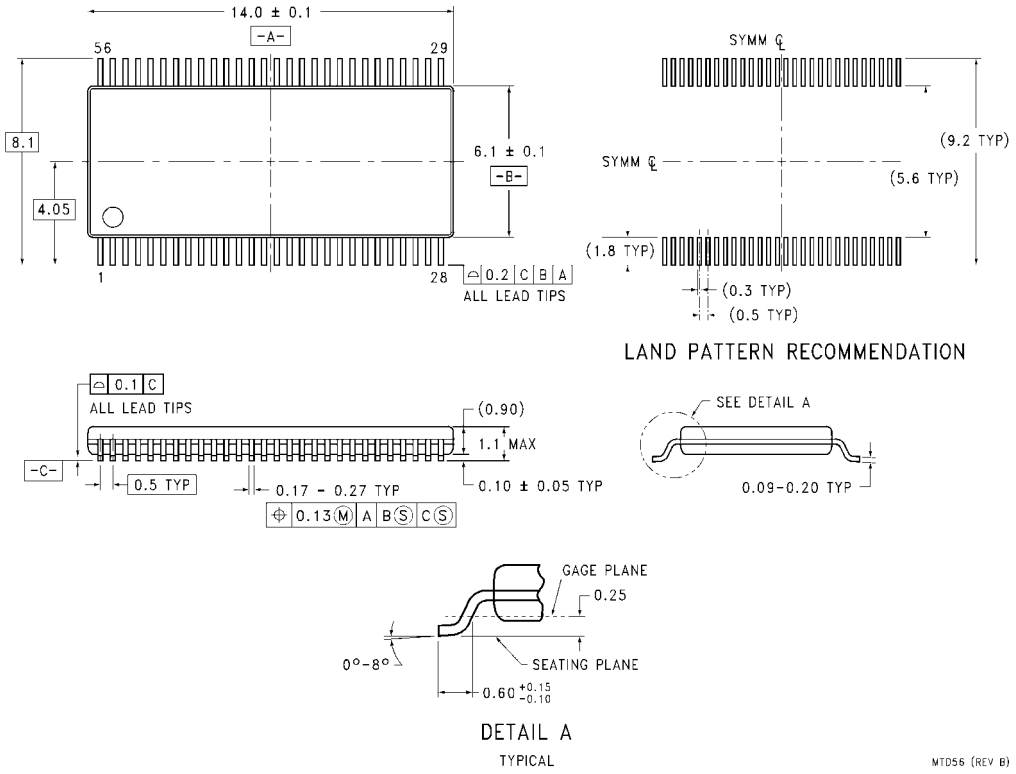
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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January 1995
Revised January 1999

74ABT16501
18-Bit Universal Bus Transceivers with 3-STATE Outputs

General Description

The ABT16501 18-bit universal bus transceiver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and $\overline{OEBA}$), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. Output-enable OEAB is active-high. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, LEBA, and CLKBA. The output enables are complementary (OEAB is active HIGH and $\overline{OEBA}$ is active LOW).

To ensure the high-impedance state during power up or power down, OE inputs should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Features

- Combines D-Type latches and D-Type flip-flops for operation in transparent, latched, or clocked mode
- Flow-through architecture optimizes PCB layout
- Guaranteed latch-up protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

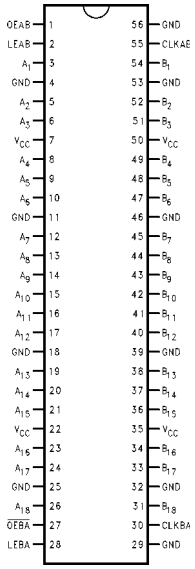
Ordering Code:

Order Number	Package Number	Package Description
74ABT16501CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16501CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape or Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for SSOP



Function Table (Note 1)

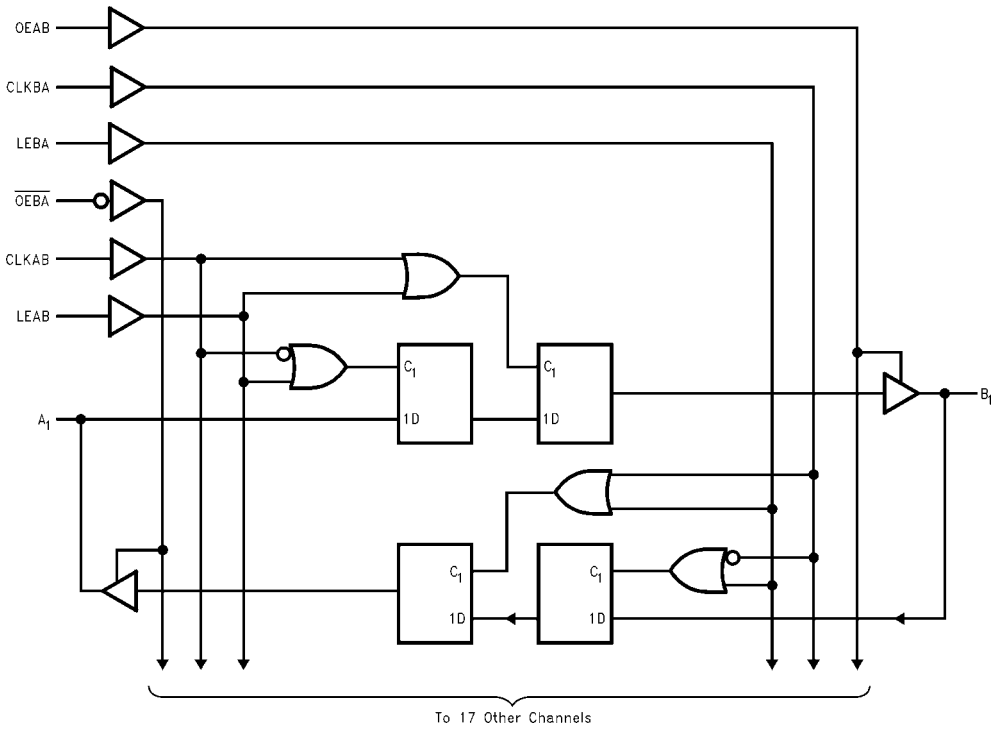
Inputs				Output
OEAB	LEAB	CLKAB	A	B
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↑	L	L
H	L	↑	H	H
H	L	H	X	B_0 (Note 2)
H	L	L	X	B_0 (Note 3)

Note 1: A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{OEBA}$, LEBA, and CLKBA.

Note 2: Output level before the indicated steady-state input conditions were established.

Note 3: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings(Note 4)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 5)	−0.5V to +7.0V
Input Current (Note 5)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disabled or Power-off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 4: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 5: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.5			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			1	μA	Max	V_{IN} = 2.7V (Note 6)
				1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−1	μA	Max	V_{IN} = 0.5V (Note 6)
				−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{IH} + I_{OZH}	Output Leakage Current			10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}$, OE = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current			−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}$, OE = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current			50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			68	mA	Max	An or Bn Outputs LOW
I_{CCZ}	Power Supply Current			1.0	mA	Max	$\overline{OE}_n$ = V_{CC}, All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 6)			0.23	mA/MHz	Max	Outputs Open Transparent Mode One Bit Toggling, 50% Duty Cycle

Note 6: Guaranteed, but not tested.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF; R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.2	V	5.0	T_A = 25°C (Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.5	–1.0		V	5.0	T_A = 25°C (Note 7)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 8)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	T_A = 25°C (Note 9)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 9)

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 8: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 9: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	150	200		150		MHz
t_{PLH}	Propagation Delay	1.0	2.7	4.6	1.0	4.6	ns
t_{PHL}	A or B to B or A	1.0	3.2	4.6	1.0	4.6	
t_{PLH}	Propagation Delay	1.0	3.1	5.0	1.0	5.0	ns
t_{PHL}	LEAB or LEBA to B or A	1.0	3.6	5.5	1.0	5.5	
t_{PLH}	Propagation Delay	1.0	3.4	5.3	1.0	5.3	ns
t_{PHL}	CLKAB or CLKBA to B or A	1.0	3.7	5.3	1.0	5.3	
t_{PZH}	Propagation Delay	1.5	2.7	5.6	1.5	5.6	ns
t_{PZL}	OEAB or $\overline{OEBA}$ to B or A	1.5	3.0	5.6	1.5	5.6	
t_{PHZ}	Propagation Delay	1.5	3.7	6.0	1.5	6.0	ns
t_{PLZ}	OEAB or $\overline{OEBA}$ to B or A	1.5	3.2	6.0	1.5	6.0	

AC Operating Requirements

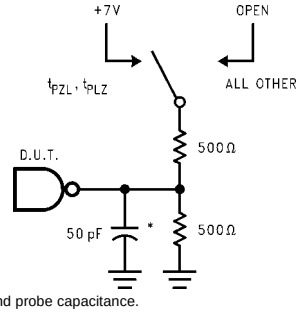
Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	
t_S(H)	Setup Time,	4.0		4.0		ns
t_S(L)	A to CLKAB, B to CLKBA	4.0		4.0		
t_H(H)	Hold Time,	0		0		ns
t_H(L)	A to CLKAB, B to CLKBA	0		0		
t_S(H)	Setup Time, A to LEAB	4.0		4.0		ns
t_S(L)	or B to LEBA, $\overline{CLK}$ HIGH	4.0		4.0		
t_H(H)	Hold Time, A to LEAB	1.5		1.5		ns
t_H(L)	or B to LEBA, $\overline{CLK}$ HIGH	1.5		1.5		
t_S(H)	Setup Time, A to LEAB	1.5		1.5		ns
t_s(L)	or B to LEBA, $\overline{CLK}$ LOW	1.5		1.5		
t_H(H)	Hold Time, A to LEAB	1.5		1.5		ns
t_H(L)	or B to LEBA, $\overline{CLK}$ LOW	1.5		1.5		
t_W(H)	Pulse Width,	3.3		3.3		ns
t_W(L)	LEAB or LEBA, HIGH	3.3		3.3		
t_W(H)	Pulse Width, CLKAB	3.3		3.3		ns
t_W(L)	or CLKBA, HIGH or LOW	3.3		3.3		

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0.0V$
$C_{I/O}$ (Note 10)	Output Capacitance	11.0	pF	$V_{CC} = 5.0V$

Note 10: $C_{I/O}$ is measured at frequency f = 1 MHz per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance.

FIGURE 1. Standard AC Test Load

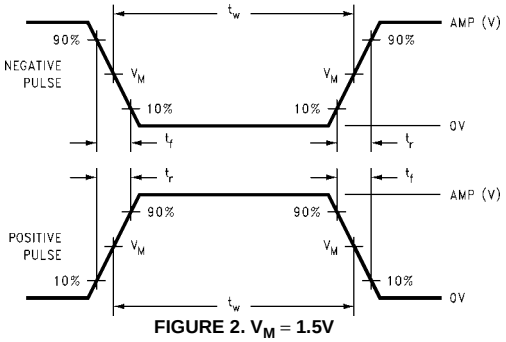


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

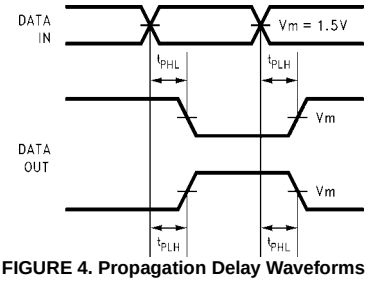


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

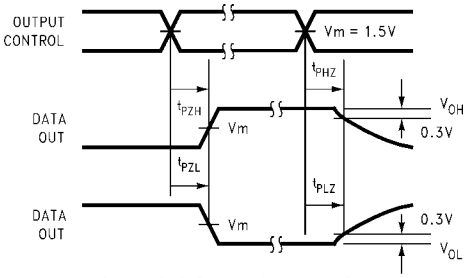


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

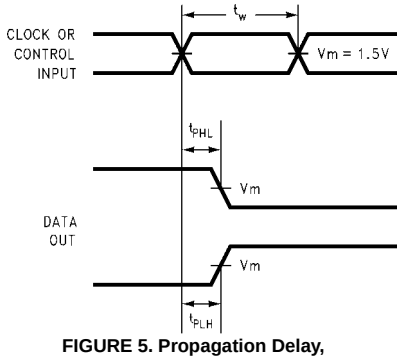


FIGURE 5. Propagation Delay, Pulse Width Waveforms

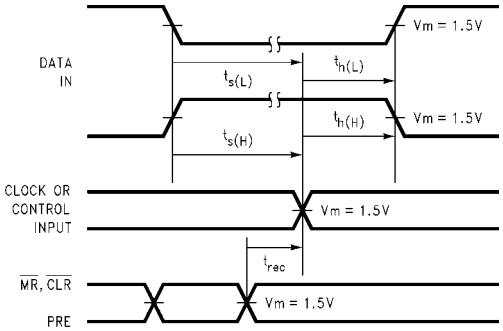
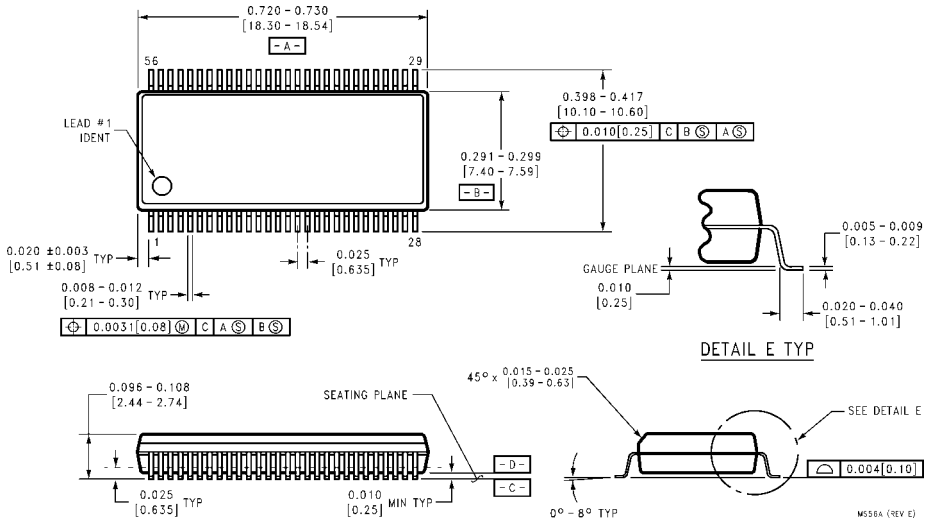


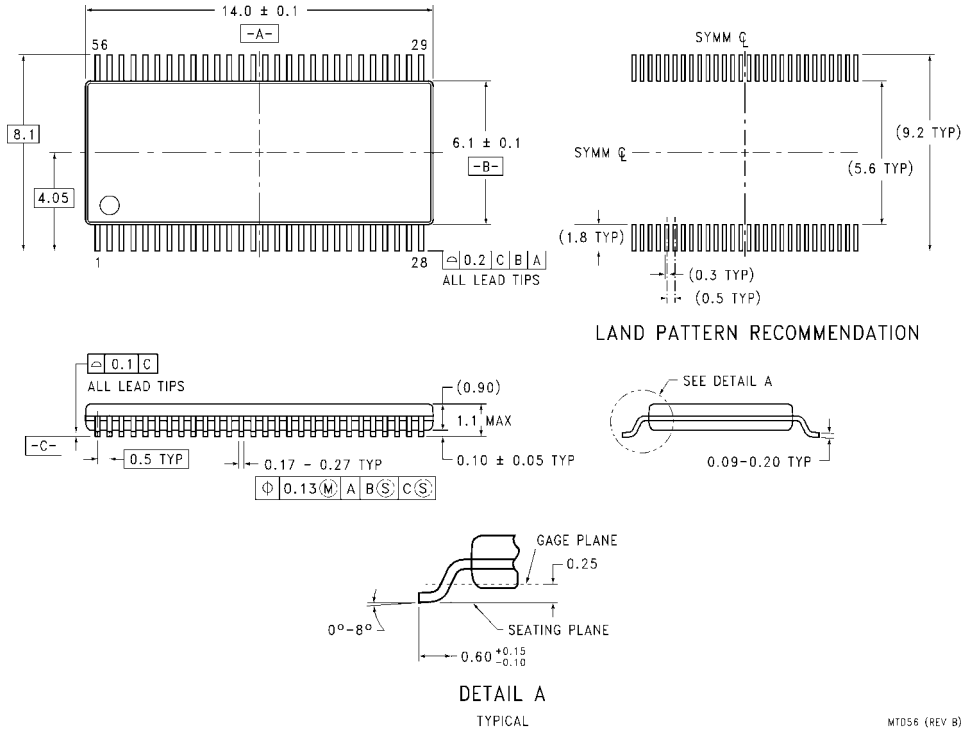
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1996
Revised November 1999

74ABT16541
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT16541 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is byte controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

Features

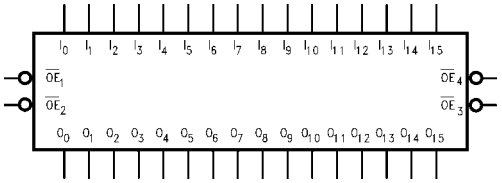
- Separate control logic for each nibble
- 16-bit version of the ABT541
- Outputs sink capability of 64 mA, source capability of 32 mA
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

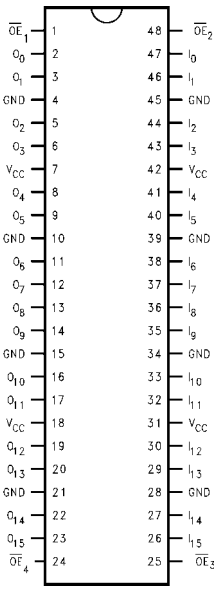
Order Number	Package Number	Package Description
74ABT16541CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16541CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active Low)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_7	O_0–O_7
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

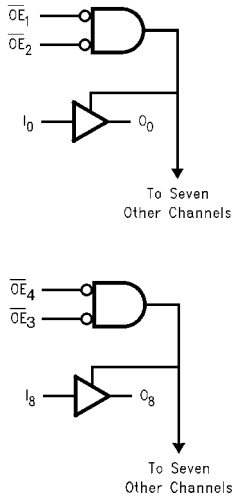
Inputs			Outputs
$\overline{OE}_4$	$\overline{OE}_3$	I_8–I_{15}	O_8–O_{15}
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The ABT16541 contains sixteen non-inverting buffers with 3-STATE outputs. The device is byte (8 bits) controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH		2.5			V	Min	I_{OH} = −3 mA
	Voltage		2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0–5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0–5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V All Other Pins GND
I_{CCH}	Power Supply Current				100	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				100	μA	Max	$\overline{OE}_n$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA		V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA	Max	Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 3)	No Load			0.1	mA/ MHz	Max	Outputs Open, $\overline{OE}_n$ = GND One Bit Toggling, 50% Duty Cycle
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}			0.4	0.7	V	5.0	T_A = 25°C (Note 4)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}		−1.3	−1.0		V	5.0	T_A = 25°C (Note 4)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage		2.7	3.0		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage		2.0	1.4		V	5.0	T_A = 25°C (Note 5)

DC Electrical Characteristics (Continued)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 5)

Note 3: Guaranteed but not tested.

Note 4: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 5: Max number of data inputs (n) switching. n-1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	T_A=+25°C, V_{CC}=+5V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	1.0	2.3	3.4	1.0	3.4	ns
t_{PHL}	Delay Data to Outputs	1.0	2.7	3.9	1.0	3.9	
t_{PZH}	Output Enable	1.5	3.5	5.2	1.5	5.2	ns
t_{PZL}	Time	1.5	3.5	6.0	1.5	6.0	
t_{PHZ}	Output Disable	1.0	4.2	5.1	1.0	5.1	ns
t_{PLZ}	Time	1.0	3.2	5.1	1.0	5.1	

Extended AC Electrical Characteristics

Symbol	Parameter	−40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 16 Outputs Switching (Note 7)			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 8)		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 16 Outputs Switching (Note 9)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Maximum Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.0	ns
t_{PHL}	Data to Outputs	1.5		5.3	1.5	6.0	2.5	8.0	
t_{PZH}	Output Enable	1.5		6.5	2.5	7.8	2.5	9.5	ns
t_{PZL}	Time	1.5		6.5	2.5	7.8	2.5	8.5	
t_{PHZ}	Output Disable	1.0		6.7	(Note 10)		(Note 10)		ns
t_{PLZ}	Time	1.0		6.7					

Note 7: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 8: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 9: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 10: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 16 Outputs Switching (Note 11) Max	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 16 Outputs Switching (Note 12) Max	Units
t_{OSHL} (Note 13)	Pin to Pin Skew HL Transitions	1.0	1.5	ns
t_{OSLH} (Note 13)	Pin to Pin Skew LH Transitions	1.0	1.5	ns
t_{PS} (Note 14)	Duty Cycle LH–HL Skew	1.5	1.5	ns
t_{OST} (Note 13)	Pin to Pin Skew LH/HL Transitions	1.7	2.0	ns
t_{PV} (Note 15)	Device to Device Skew LH/HL Transitions	2.0	2.5	ns

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 12: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 14: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

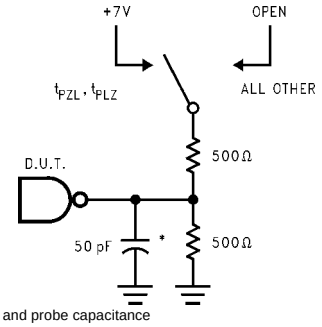
Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 5.0V$
C_{OUT} (Note 16)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 16: C_{OUT} is measured at frequency f = 1 MHz; per MIL STD-883, Method 3012.

AC Loading



* Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

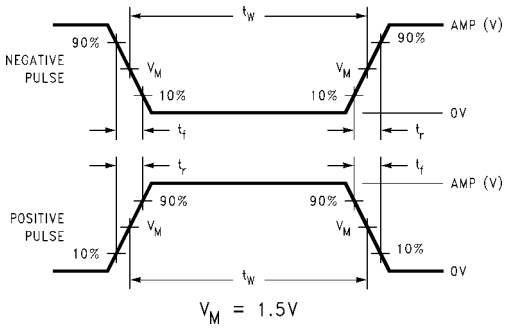


FIGURE 2. Test Input Pulse Requirements

Amplitude	Rep Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

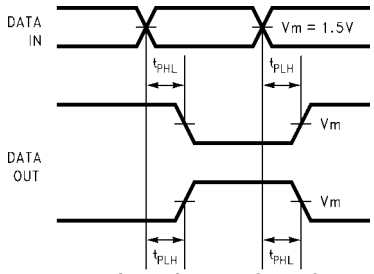


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

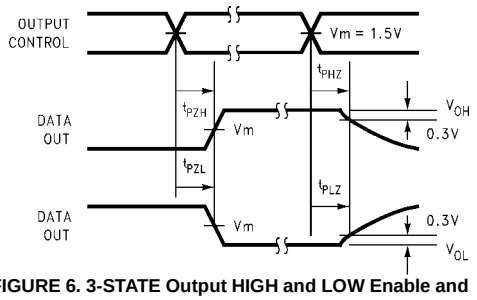


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

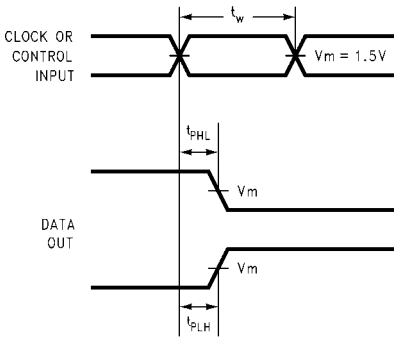


FIGURE 5. Propagation Delay, Pulse Width Waveforms

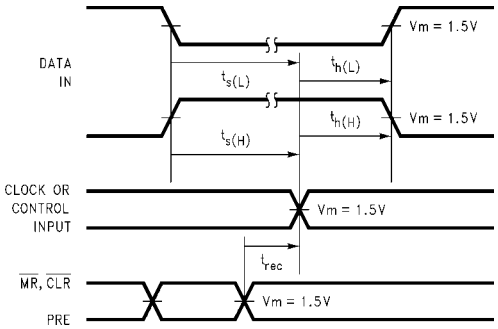
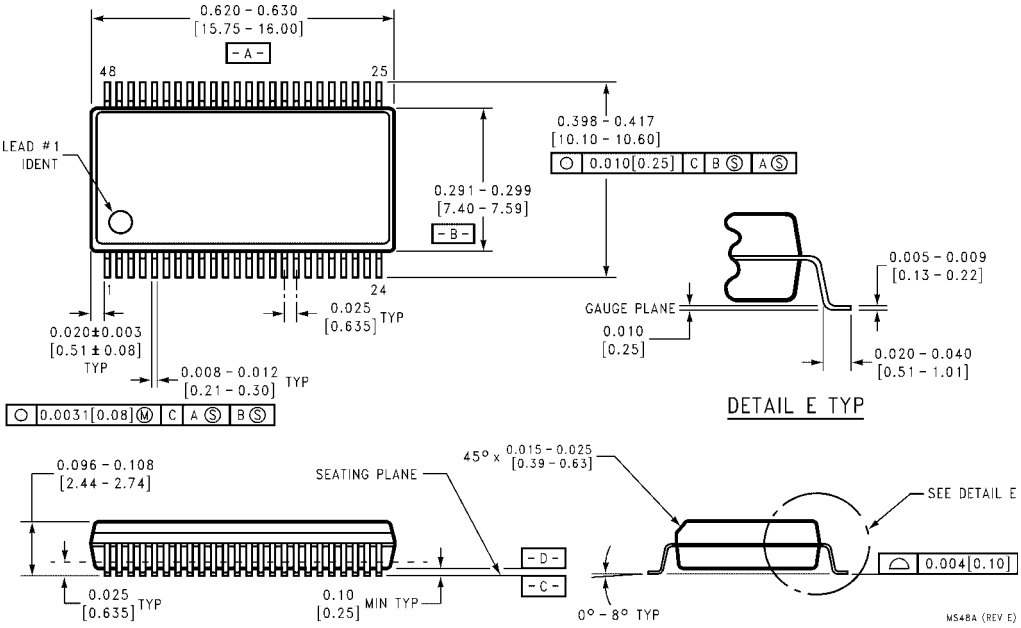


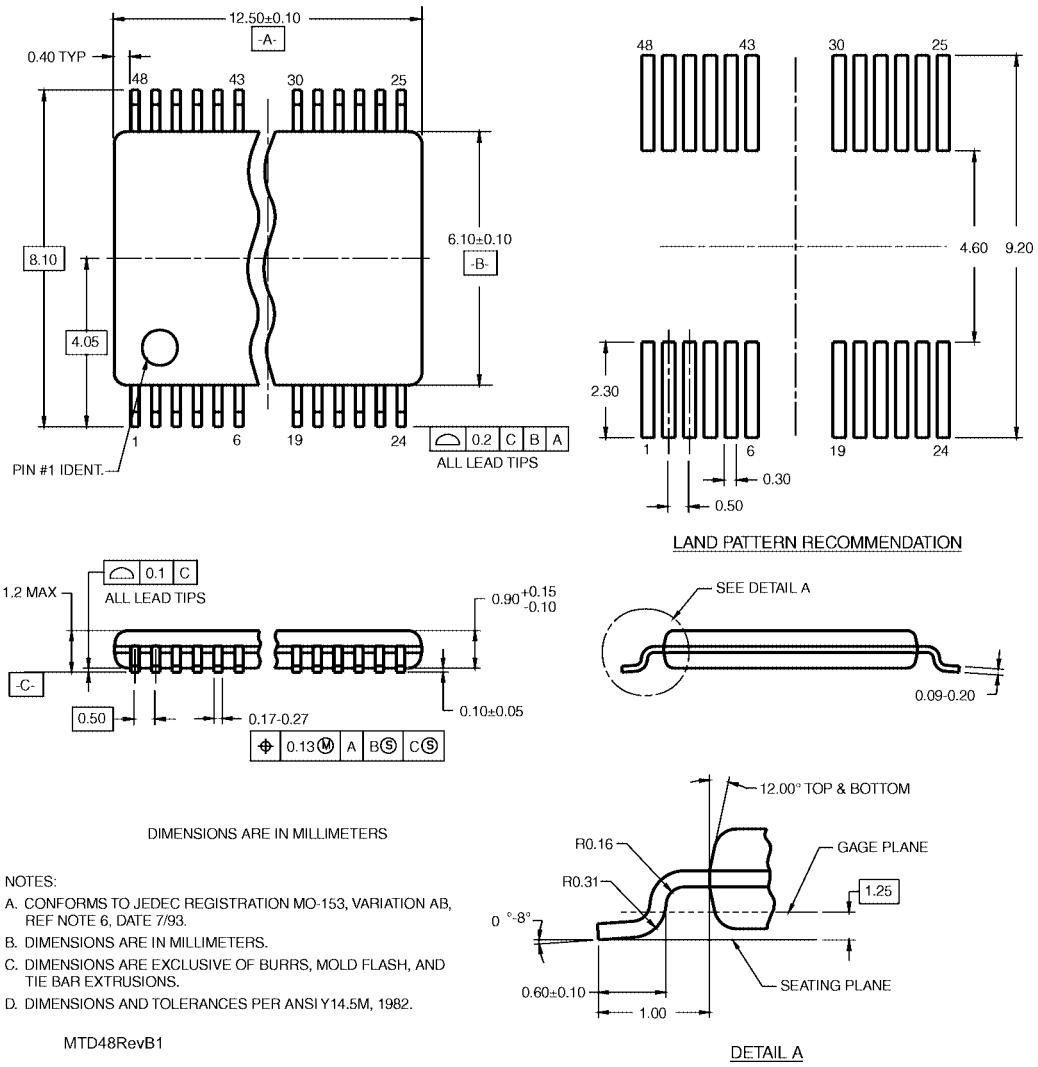
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1993
Revised January 1999

74ABT16543
16-Bit Registered Transceiver with 3-STATE Outputs

General Description

The ABT16543 16-bit transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. Each byte has separate control inputs, which can be shorted together for full 16-bit operation.

Features

- Back-to-back registers for storage
- Bidirectional data path
- A and B outputs have current sourcing capability of 32 mA and current sinking capability of 64 mA
- Separate control logic for each byte
- 16-bit version of the ABT543
- Separate controls for data flow in each direction
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

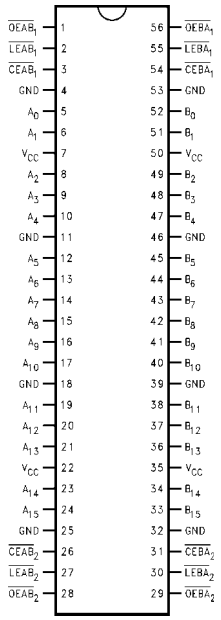
Ordering Code:

Order Number	Package Number	Package Description
74ABT16543CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16543CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

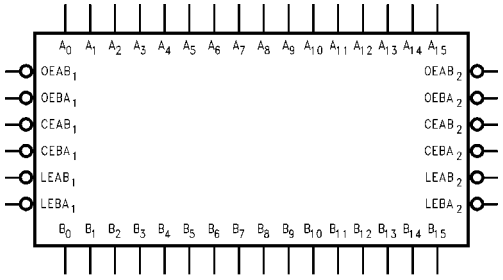
Pin Assignment for SSOP and TSSOP



Pin Descriptions

Pin Names	Description
$\overline{OEAB}_n$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}_n$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}_n$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}_n$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}_n$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}_n$	B-to-A Latch Enable Input (Active LOW)
A_0–A_{15}	A-to-B Data Inputs or
	B-to-A 3-STATE Outputs
B_0–B_{15}	B-to-A Data Inputs or
	A-to-B 3-STATE Outputs

Logic Symbol



Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}_n$	$\overline{LEAB}_n$	$\overline{OEAB}_n$	(Byte n)	(Byte n)
H	X	X	Latched	HIGH Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	HIGH Z
L	X	L	—	Driving

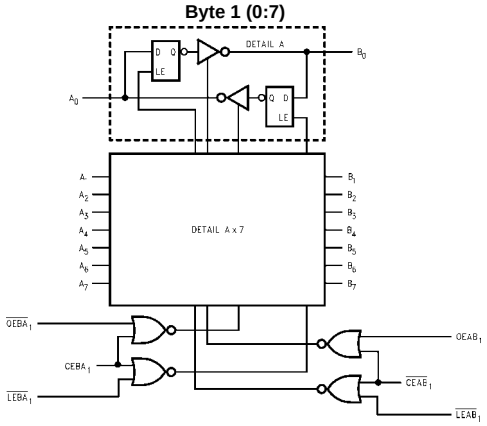
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown;
B-to-A flow control is the same, except using $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$

Functional Description

The ABT16543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable ($\overline{CEAB}$) input must be low in order to enter data from the A port or take data from the B-Port as indicated in the Data I/O Control Table. With $\overline{CEAB}$ low, a low signal on ($\overline{LEAB}$) input makes the A to B latches transparent; a subsequent low to high transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both low, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$. Each byte has separate control inputs, allowing the device to be used as two 8-bit transceivers or as one 16-bit transceiver.

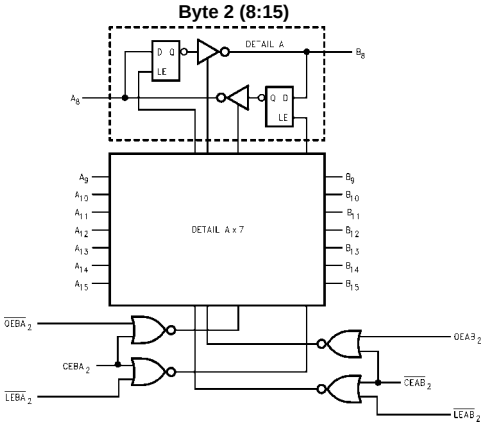
Logic Diagrams

Byte 1 (0:7)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disable or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5					I_{OH} = −3 mA, (A_n, B_n)
		2.0					I_{OH} = −32 mA, (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA, (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins)
							All Other Pins Grounded
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) ((Note 3)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 3)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OEAB}$ or $\overline{CEAB}$ = 2V
I_{IL} + I_{OZL}	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OEAB}$ or $\overline{CEAB}$ = 2V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			1.0	mA	Max	Outputs 3-STATE
							All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V
							All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 3)			0.25	mA/MHz	Max	Outputs Open, $\overline{CEAB}$, $\overline{OEAB}$, $\overline{LEAB}$ = GND, $\overline{CEBA}$ = V_{CC}, One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed but not tested.

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n to B_n or B_n to A_n	1.5	3.0	5.7	1.5	5.7	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEAB_n}$ to B_n, $\overline{LEBA_n}$ to A_n	1.5	3.0	5.5	1.5	5.5	ns
t_{PZH} t_{PZL}	Enable Time $\overline{OEBA_n}$ or $\overline{OEAB_n}$ to A_n or B_n	1.5	2.8	5.2	1.5	5.2	ns
t_{PHZ} t_{PLZ}	Disable Time $\overline{OEAB_n}$ or $\overline{OEBA_n}$ to A_n or B_n	1.6	3.1	6.0	1.6	6.0	ns
t_{PZH} t_{PZL}	Enable Time $\overline{CEBA_n}$ or $\overline{CEAB_n}$ to A_n or B_n	1.5	3.1	6.2	1.5	6.2	ns
t_{PHZ} t_{PLZ}	Disable Time $\overline{CEBA_n}$ or $\overline{CEAB_n}$ to A_n or B_n	1.7	3.2	6.3	1.7	6.3	ns

AC Operating Requirements

(SSOP Package)

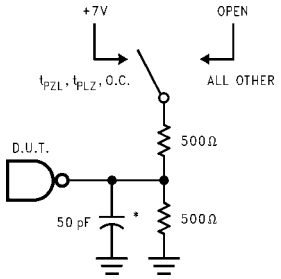
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -55°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW A_n or B_n to $\overline{LEBA_n}$ or $\overline{LEAB_n}$	2.0 2.0		2.0 2.0		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW A_n or B_n to $\overline{LEBA_n}$ or $\overline{LEAB_n}$	1.0 1.0		1.0 1.0		ns
$t_W(L)$	Pulse Width, LOW	3.0		3.0		ns

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$ (non I/O pins)
$C_{I/O}$ (Note 4)	Output Capacitance	11.0	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 4: $C_{I/O}$ is measured at frequency, f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

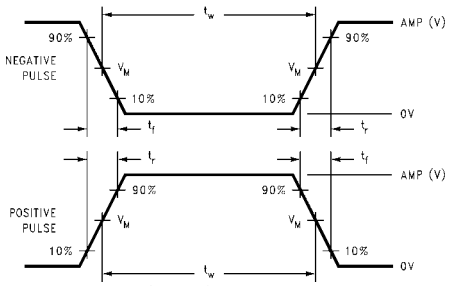


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

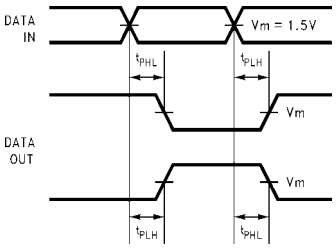


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

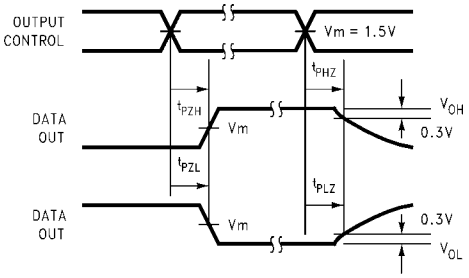


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

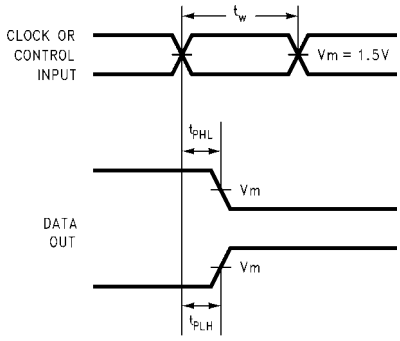


FIGURE 5. Propagation Delay, Pulse Width Waveforms

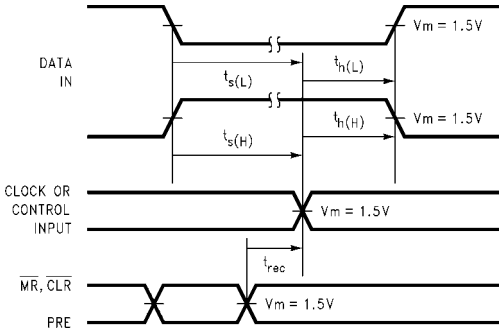
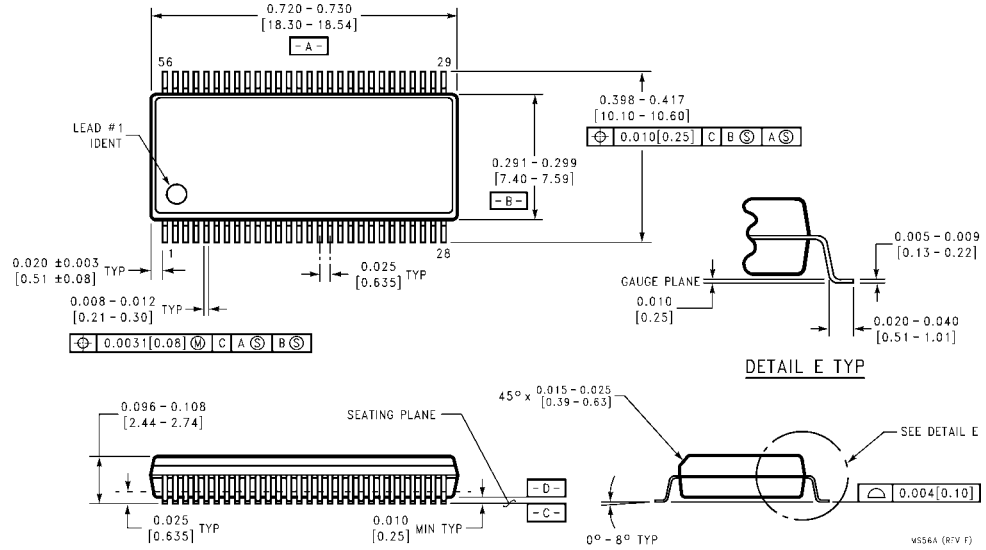


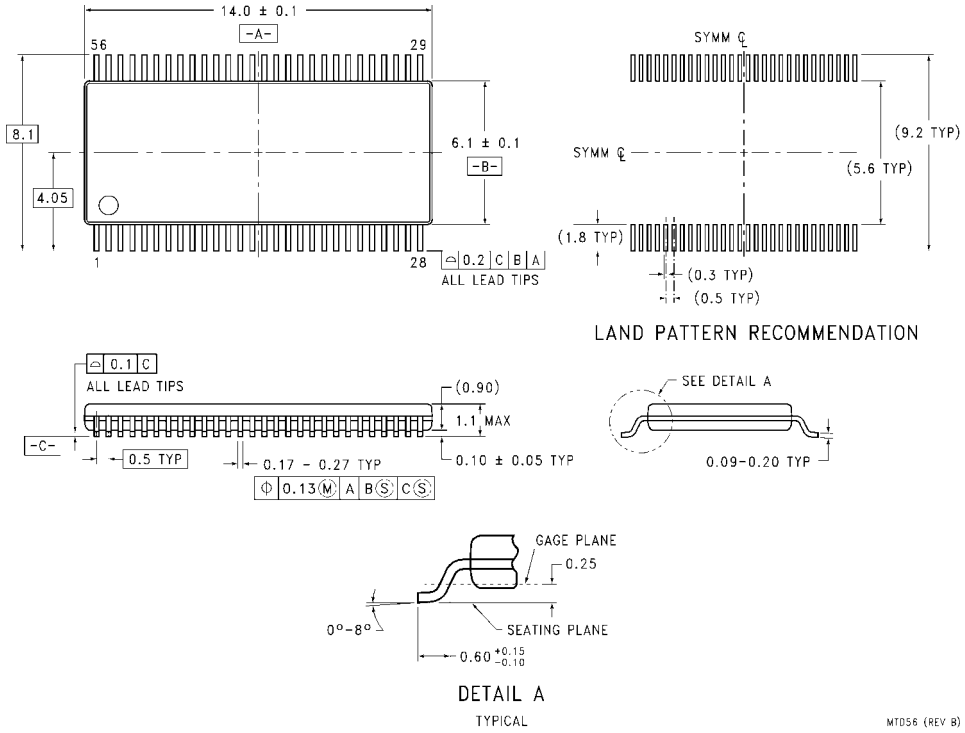
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1993
Revised November 1999

74ABT16646
16-Bit Transceivers and Registers with 3-STATE Outputs

General Description

The ABT16646 consists of bus transceiver circuits with 3-STATE, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a high logic level. Control $\overline{OE}$ and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control $\overline{OE}$ is Active LOW. In the isolation mode (control $\overline{OE}$ HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

Features

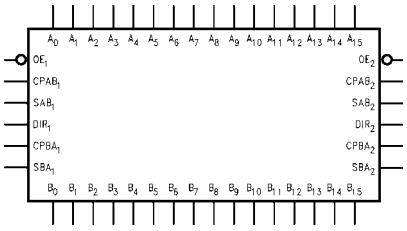
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

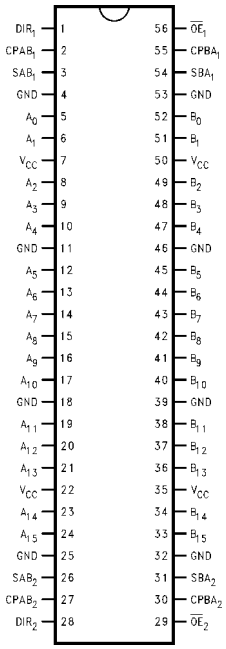
Order Number	Package Number	Package Description
74ABT16646CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16646CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_{15}	Data Register A Inputs/ 3-STATE Outputs
B_0–B_{15}	Data Register B Inputs/ 3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
$\overline{OE}_n$	Output Enable Input
DIR	Direction Control Input

Function Table

Inputs						Data I/O (Note 1)		Output Operation Mode
$\overline{OE}_1$	DIR_1	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_{0-7}	B_{0-7}	
H	X	H or L	H or L	X	X			Isolation
H	X	⌐	X	X	X	Input	Input	Clock An Data into A Register
H	X	X	⌐	X	X			Clock Bn Data Into B Register
L	H	X	X	L	X			An to Bn—Real Time (Transparent Mode)
L	H	⌐	X	L	X	Input	Output	Clock An Data to A Register
L	H	H or L	X	H	X			A Register to Bn (Stored Mode)
L	H	⌐	X	H	X			Clock An Data into A Register and Output to Bn
L	L	X	X	X	L			Bn to An—Real Time (Transparent Mode)
L	L	X	⌐	X	L	Output	Input	Clock Bn Data into B Register
L	L	X	H or L	X	H			B Register to An (Stored Mode)
L	L	X	⌐	X	H			Clock Bn into B Register and Output to An

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

Real Time Transfer A-Bus to B-Bus

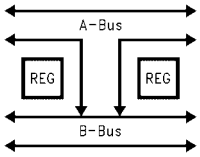


FIGURE 1.

Real Time Transfer B-Bus to A-Bus

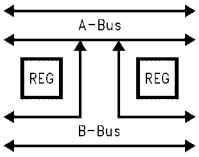


FIGURE 2.

Storage from Bus to Register

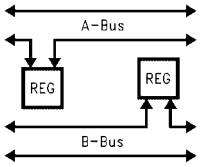


FIGURE 3.

Transfer from Register to Bus

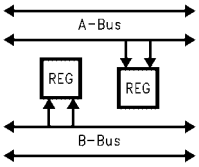
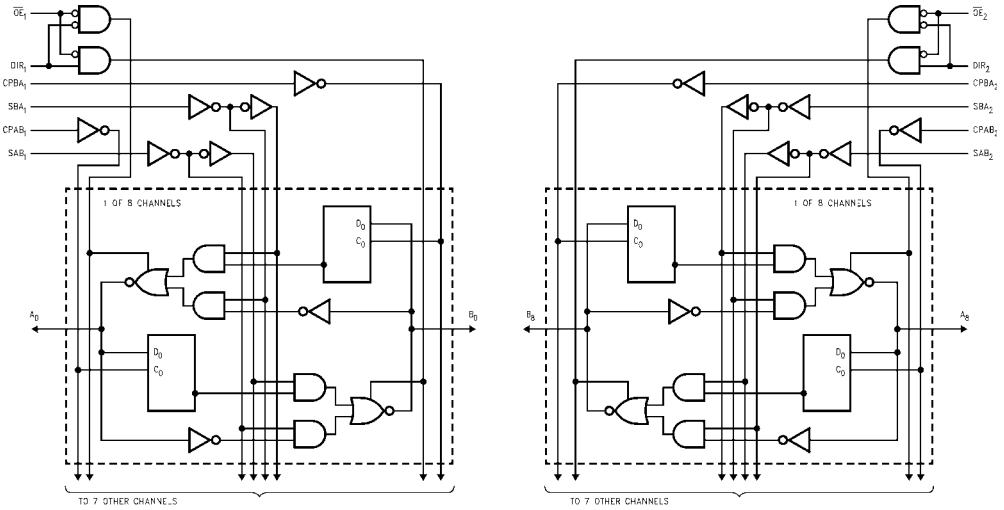


FIGURE 4.

Logic Diagram



Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable or	
Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5					I_{OH} = −3 mA, (A_n, B_n)
		2.0					I_{OH} = −32 mA, (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA, (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins)
							All Other Pins Grounded
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 5)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 5)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OE}$ = 2.0V
$I_{IL} + I_{OZL}$	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n);
							All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			1.0	mA	Max	Outputs 3-STATE; All Others GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V
							All Other Outputs at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load				mA/	Max	Outputs OPEN
	(Note 5)			0.23	MHz		$\overline{OE}$, DIR, and SEL = GND,
							Non-I/O = GND or V_{CC}(Note 4)
							One Bit toggling, 50% duty cycle

Note 4: For 8-bit toggling, I_{CCD} < 1.4 mA/MHz.

Note 5: Guaranteed but not tested.

DC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.2	V	5.0	T_A = 25°C (Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.4	−1.0		V	5.0	T_A = 25°C (Note 6)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25° (Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.6		V	5.0	T_A = 25°C (Note 8)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 8)

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 8: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		200				MHz
t_{PLH}	Propagation Delay	1.5	3.0	4.9	1.5	4.9	ns
t_{PHL}	Clock to Bus	1.5	3.4	4.9	1.5	4.9	
t_{PLH}	Propagation Delay	1.5	2.6	4.5	1.5	4.5	ns
t_{PHL}	Bus to Bus	1.5	3.0	4.5	1.5	4.5	
t_{PLH}	Propagation Delay	1.5	2.9	5.0	1.5	5.0	ns
t_{PHL}	SBA_n or SAB_n to A_n to B_n	1.5	3.2	5.0	1.5	5.0	
t_{PZH}	Enable Time	1.5	2.8	5.5	1.5	5.5	ns
t_{PZL}	$\overline{OE}_n$ to A_n or B_n	1.5	3.0	5.5	1.5	5.5	
t_{PHZ}	Disable Time	1.5	3.9	6.0	1.5	6.0	ns
t_{PLZ}	$\overline{OE}_n$ to A_n or B_n	1.5	3.2	6.0	1.5	6.0	
t_{PZH}	Enable Time	1.5	3.5	5.5	1.5	5.5	ns
t_{PZL}	DIR_n to A_n or B_n	1.5	3.2	5.5	1.5	5.5	
t_{PHZ}	Disable Time	1.5	3.8	6.5	1.5	6.5	ns
t_{PLZ}	DIR_n to A_n or B_n	1.5	3.2	6.5	1.5	6.5	

AC Operating Requirements

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	
t_S(H)	Setup Time, HIGH	2.0		2.0		ns
t_S(L)	or LOW Bus to Clock					
t_H(H)	Hold Time, HIGH	1.0		1.0		ns
t_H(L)	or LOW Bus to Clock					
t_W(H)	Pulse Width,	3.0		3.0		ns
t_W(L)	HIGH or LOW					

Extended AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 9)		$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 1 Output Switching (Note 10)		$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 11)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.8	2.0	7.5	2.5	10.0	ns
t_{PHL}	Clock to Bus	1.5	5.8	2.0	7.5	2.5	10.0	
t_{PLH}	Propagation Delay	1.5	6.5	2.0	7.0	2.5	9.5	ns
t_{PHL}	Bus to Bus	1.5	6.5	2.0	7.0	2.5	9.5	
t_{PLH}	Progagation Delay	1.5	6.0	2.0	7.5	2.5	10.0	ns
t_{PHL}	SBA_n or SAB_n to A_n or B_n	1.5	6.0	2.0	7.5	2.5	10.0	
t_{PZH}	Output Enable Time	1.5	6.0	2.0	8.0	2.5	10.5	ns
t_{PZL}	$\overline{OE}_n$ to A_n or B_n	1.5	6.0	2.0	8.0	2.5	10.5	
t_{PHZ}	Output Disable Time	1.5	6.0	(Note 12)		(Note 12)		ns
t_{PLZ}	$\overline{OE}_n$ to A_n or B_n	1.5	6.0					
t_{PZH}	Output Enable Time	1.5	6.5	2.0	8.0	2.5	10.5	ns
t_{PZL}	DIR to A_n or B_n	1.5	6.5	2.0	8.0	2.5	10.5	
t_{PHZ}	Output Disable Time	1.5	6.5	(Note 12)		(Note 12)		ns
t_{PLZ}	DIR to A_n or B_n	1.5	6.5					

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 12: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 16 Outputs Switching (Note 13)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 16 Outputs Switching (Note 14)	Units
		Max	Max	
t_{OSHL} (Note 15)	Pin to Pin Skew HL Transitions	2.0	2.5	ns
t_{OSLH} (Note 15)	Pin to Pin Skew LH Transitions	2.0	2.5	ns
t_{PS} (Note 16)	Duty Cycle LH–HL Skew	2.0	2.5	
t_{OST} (Note 15)	Pin to Pin Skew LH/HL Transitions	2.8	3.0	ns
t_{PV} (Note 17)	Device to Device Skew LH/HL Transitions	3.5	4.0	ns

Note 13: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 14: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}). This specification is guaranteed but not tested.

Note 16: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

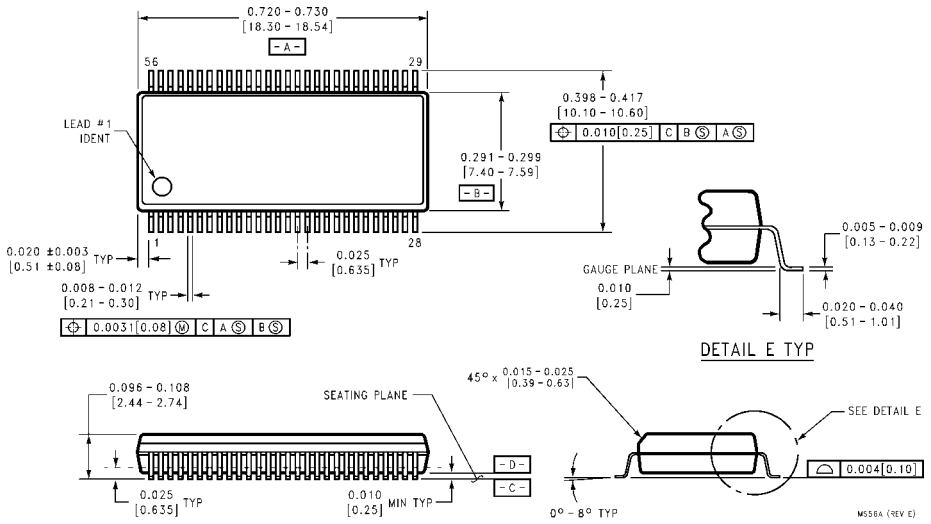
Note 17: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$ (non I/O pins)
$C_{I/O}$ (Note 18)	Output Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n)

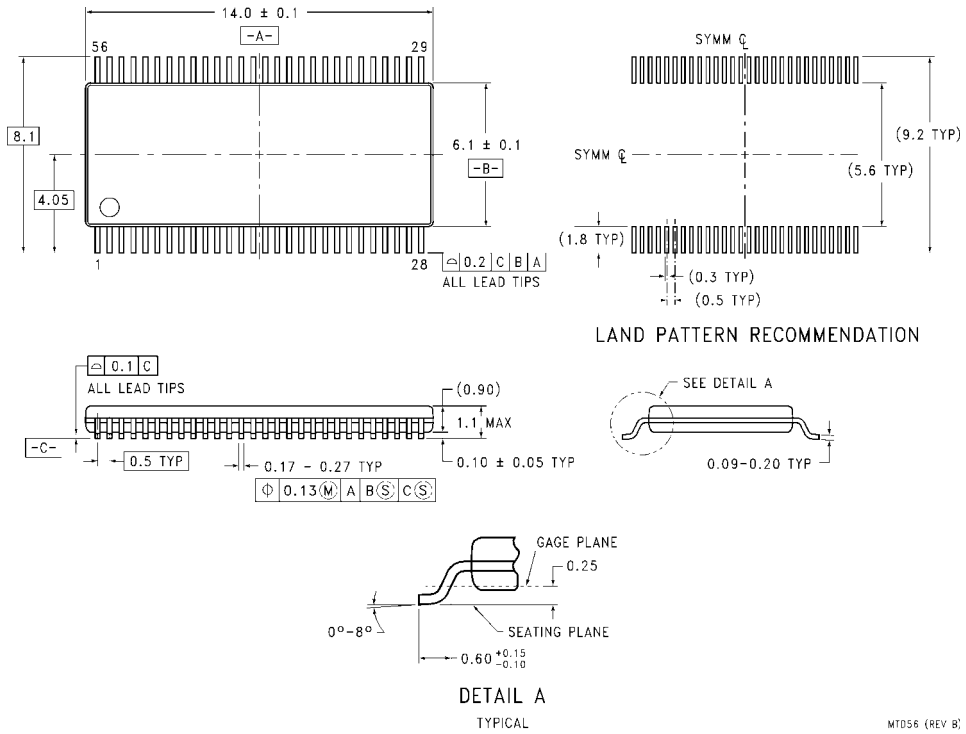
Note 18: $C_{I/O}$ is measured at frequency, f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

April 1993
Revised January 1999

74ABT16652
16-Bit Transceivers and Registers with 3-STATE Outputs

General Description

The ABT16652 consists of sixteen bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function.

Features

- Independent registers for A and B buses
- Multiplexed real-time and stored data
- Separate control logic for each byte
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

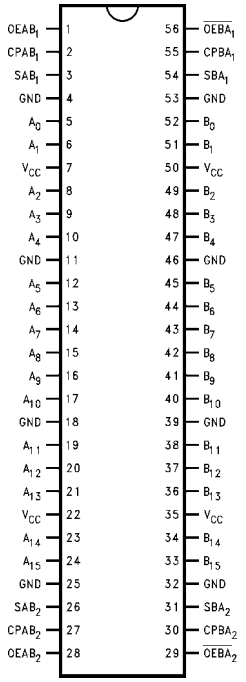
Order Number	Package Number	Package Description
74ABT16652CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16652CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pin Descriptions

Pin Names	Descriptions
A_0–A_{16}	Data Register A Inputs/ 3-STATE Outputs
B_0–B_{16}	Data Register B Inputs/ 3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
$OEAB_n$, $\overline{OEBA}_n$	Output Enable Inputs

Connection Diagram



Functional Description

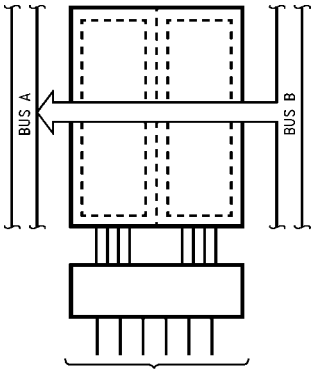
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB_n, SBA_n) controls can multiplex stored and real-time.

The examples in *Figure 1* demonstrate the four fundamental bus-management functions that can be performed with the ABT16652.

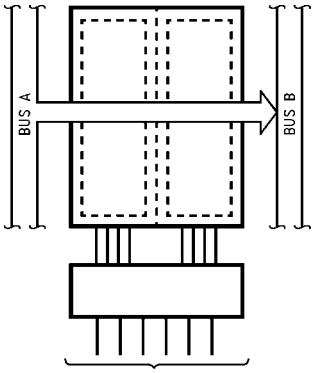
Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs ($CPAB_n$, $CPBA_n$) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling $OEAB_n$ and $\overline{OEBA}_n$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Note A: Real-Time Transfer Bus B to Bus A



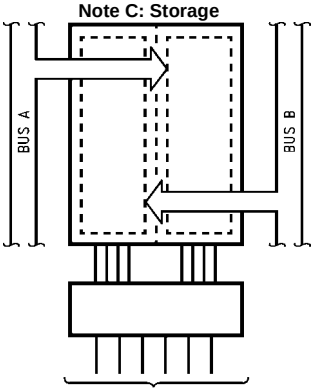
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
1	1	1	1	1	1
L	L	X	X	X	L

Note B: Real-Time Transfer Bus A to Bus B



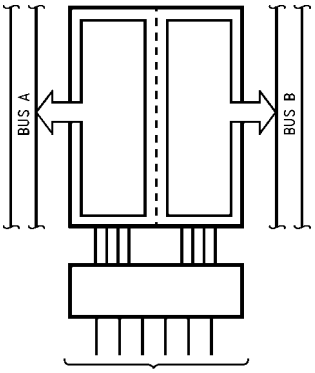
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
1	1	1	1	1	1
H	H	X	X	L	X

Note C: Storage



OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
1	1	1	1	1	1
X	H	↑	X	X	X
L	X	X	↑	X	X
L	H	↑	↑	X	X

Note D: Transfer Storage Data to A or B



OEAB	$\overline{OEBA}$	$CPAB_1$	CPBA	SAB	SBA
1	1		1	1	1
H	L	H or L	H or L	H	H

FIGURE 1.

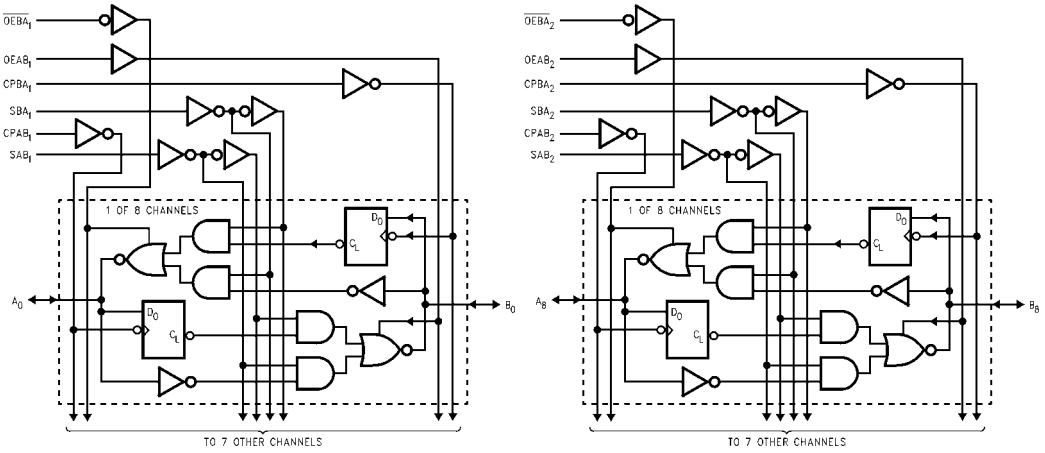
Function Table

Inputs						Inputs/Outputs (Note 1)		Operating Mode
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW to HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW to HIGH transition on the clock inputs. This also applies to data I/O (A and B: 8–15) and #2 control pins.

Logic Diagrams



Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disable or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage				V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5			V	Min	I_{OH} = −3 mA, (A_n, B_n)
		2.0					I_{OH} = −32 mA, (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA, (A_n, B_n)
V_{ID}	Input Leakage Test				V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins) All Other Pins Grounded
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 4)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 4)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $OEAB_n$ = GND and $\overline{OEBA}_n$ = 2.0V
$I_{IL} + I_{OZL}$	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $OEAB_n$ = GND and $\overline{OEBA}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current			−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			1.0	mA	Max	Outputs 3-STATE; All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 4)			0.23	mA/MHz	Max	Outputs Open $OEAB_n$, $\overline{OEBA}_n$ and SEL = GND Non-I/O = GND or V_{CC} One bit toggling, 50% duty cycle

Note 4: Guaranteed but not tested.

DC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.2	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.4	–1.0		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25° (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.6		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	3.0	4.9	1.5	4.9	ns
t_{PHL}	Clock to Bus	1.5	3.4	4.9	1.5	4.9	
t_{PLH}	Propagation Delay	1.5	2.6	4.5	1.5	4.5	ns
t_{PHL}	Bus to Bus	1.5	3.0	4.5	1.5	4.5	
t_{PLH}	Propagation Delay	1.5	2.9	5.0	1.5	5.0	ns
t_{PHL}	SBA_n or SAB_n	1.5	3.2	5.0	1.5	5.0	
	to A_n to B_n						
t_{PZH}	Enable Time	1.5	2.8	5.5	1.5	5.5	ns
t_{PZL}	$\overline{OEBA}_n$ or $OEAB_n$	1.5	3.0	5.5	1.5	5.5	
	to A_n or B_n						
t_{PHZ}	Disable Time	1.5	3.9	5.9	1.5	5.9	ns
t_{PLZ}	$\overline{OEBA}_n$ or $OEAB_n$	1.5	3.3	5.9	1.5	5.9	
	to A_n or B_n						

AC Operating Requirements

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f_{max}	Max Clock Frequency		200				MHz
t_S(H)	Setup Time, HIGH	2.0			2.0		ns
t_S(L)	or LOW Bus to Clock						
t_H(H)	Hold Time, HIGH	1.0			1.0		ns
t_H(L)	or LOW Bus to Clock						
t_W(H)	Pulse Width,	3.0			3.0		ns
t_W(L)	HIGH or LOW						

Extended AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 16 Outputs Switching (Note 8)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 9)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 16 Outputs Switching (Note 10)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Progagation Delay	1.5	5.8	2.0	7.5	2.5	10.0	ns
t_{PHL}	Clock to Bus	1.5	5.8	2.0	7.5	2.5	10.0	
t_{PLH}	Progagation Delay	1.5	6.5	2.0	7.0	2.5	9.5	ns
t_{PHL}	Bus to Bus	1.5	6.5	2.0	7.0	2.5	9.5	
t_{PLH}	Progagation Delay	1.5	6.0	2.0	7.5	2.5	10.0	
t_{PHL}	SBA or SAB to	1.5	6.0	2.0	7.5	2.5	10.0	ns
	A_n or B_n							
t_{PZH}	Output Enable Time	1.5	6.0	2.0	8.0	2.5	10.5	
t_{PZL}	$\overline{OEBA}_n$ or $OEAB_n$ to	1.5	6.0	2.0	8.0	2.5	10.5	ns
	A_n or B_n							
t_{PHZ}	Output Disable Time	1.5	6.0					
t_{PLZ}	$\overline{OEBA}$ or OEAB to	1.5	6.0	(Note 11)		(Note 11)		ns
	A_n or B_n							

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew (Note 12)

(SSOP Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 16 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 16 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew HL Transitions	2.0	2.5	ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Transitions	2.0	2.5	ns
t_{PS} (Note 15)	Duty Cycle LH–HL Skew	2.0	2.5	
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Transitions	2.8	3.0	ns
t_{PV} (Note 16)	Device to Device Skew LH/HL Transitions	3.5	4.0	ns

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 13: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

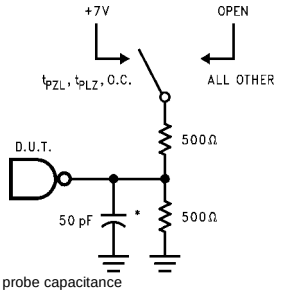
Note 16: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions (T_A = 25°C)
C_{IN}	Input Capacitance	5.0	pF	V_{CC} = 0V (non I/O pins)
$C_{I/O}$ (Note 17)	I/O Capacitance	11.0	pF	V_{CC} = 5.0V (A_n, B_n)

Note 17: $C_{I/O}$ is measured at frequency, f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 2. Standard AC Test Load

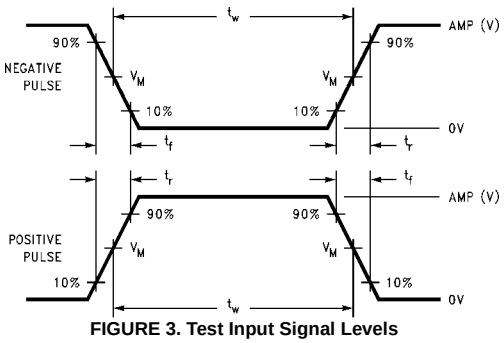


FIGURE 3. Test Input Signal Levels

Input Pulse Requirement

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 4. Test input Signal Requirements

AC Waveforms

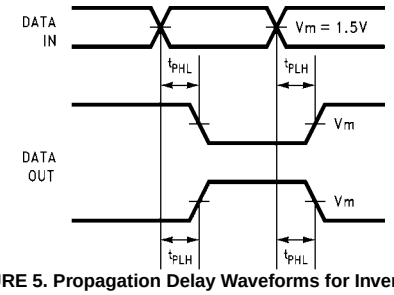


FIGURE 5. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

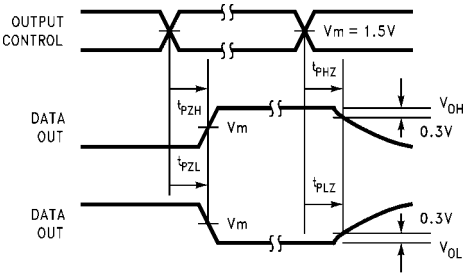


FIGURE 7. 3-STATE Output HIGH and LOW Enable and Disable Times

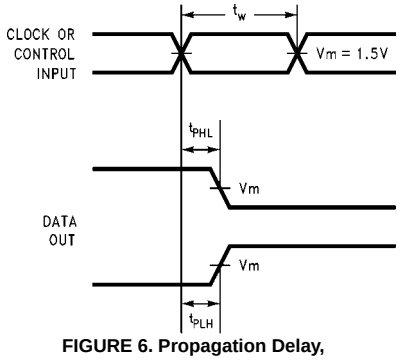


FIGURE 6. Propagation Delay, Pulse Width Waveforms

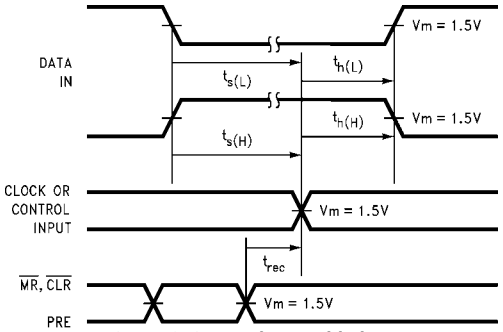
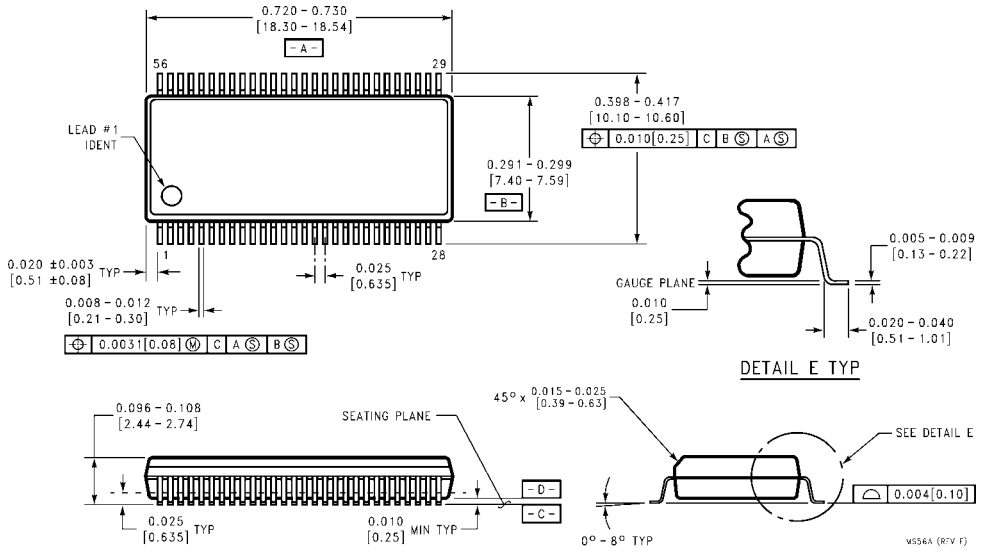


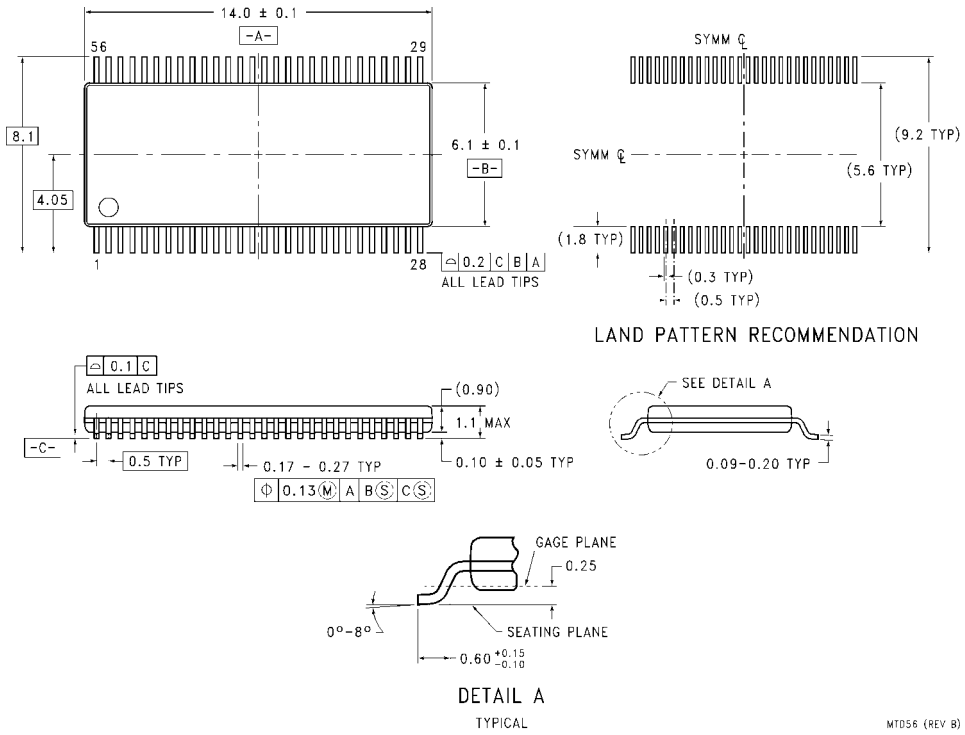
FIGURE 8. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

FAIRCHILD SEMICONDUCTOR™

November 1993
Revised January 1999

74ABT16952
16-Bit Registered Transceiver with 3-STATE Outputs

General Description

The ABT16952 is a 16-bit registered transceiver. Two 8-bit back to back registers store data flowing in both directions between two bidirectional buses. Separate clock, clock enable and 3-STATE output enable signals are provided for each register. The output pins are guaranteed to source 32 mA and to sink 64 mA.

Features

- Separate clock, clock enable and 3-STATE output enable provided for each register
- A and B output sink capability of 64 mA source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT16952CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16952CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the letter suffix "X" to the ordering code.

Pin Descriptions

Pin Names	Description
A_0–A_{15}	Data Register A Inputs/ B-Register 3-STATE Outputs
B_0–B_{15}	Data Register B Inputs/ A-Register 3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
$\overline{CEA}_n$, $\overline{CEB}_n$	Clock Enable
$\overline{OEAB}_n$, $\overline{OEBA}_n$	Output Enable Inputs

Output Control

$\overline{OE}$	Internal Q	Output	Function
H	X	Z	Disable Outputs
L	L	L	Enable Outputs
L	H	H	

Register Function Table

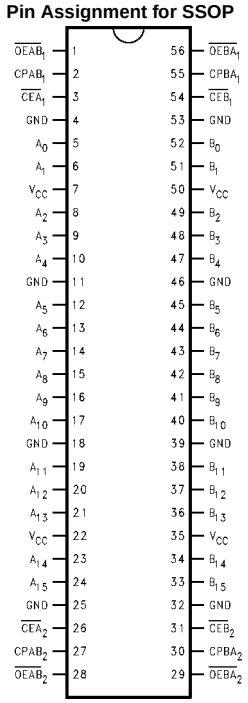
(Applies to A or B Register)

Inputs			Internal	
D	CP	$\overline{CE}$	Q	Function
X	X	H	NC	Hold Data
L	↗	L	L	Load Data
H	↗	L	H	

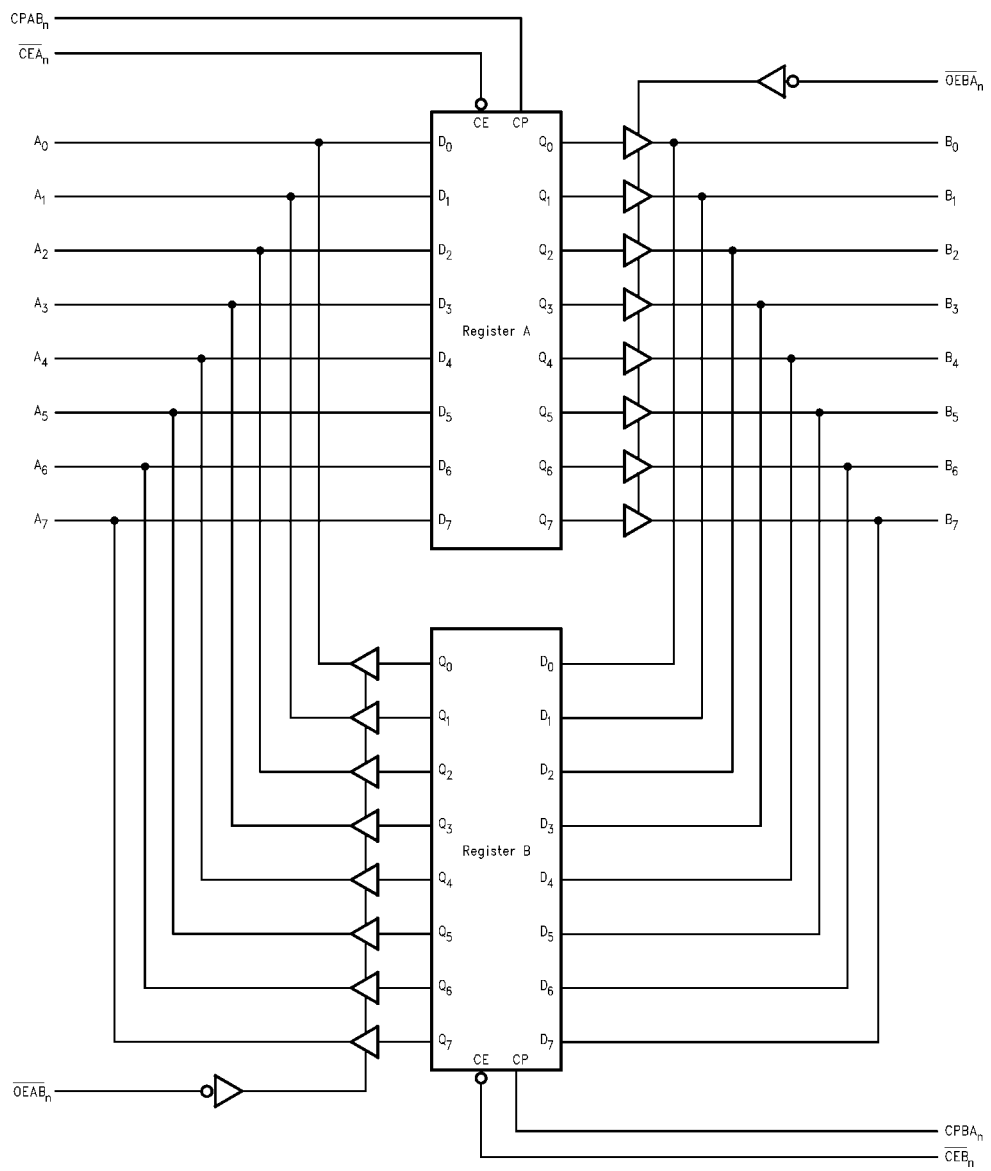
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance
↗ = LOW-to-HIGH Transition
NC = No Change

Connection Diagram

Pin Assignment for SSOP



Block Diagram



n for either byte 1 or byte 2

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disable or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5					I_{OH} = −3 mA (A_n, B_n)
		2.0					I_{OH} = −32 mA (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55			I_{OL} = 64 mA (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA (Non-I/O Pins) All Other Pins Grounded
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 4)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 4)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OEA}$ or $\overline{OEB}$ = 2.0V
$I_{IL} + I_{OZL}$	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OEA}$ or $\overline{OEB}$ = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			1.0	mA	Max	Outputs 3-STATE; All Others GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V; All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 4)			0.18	mA/MHz	Max	Outputs Open $\overline{OEA}$ or $\overline{OEB}$ = GND, Non-I/O = GND or V_{CC} One Bit toggling, 50% duty cycle (Note 3)

Note 3: For 8-bit toggling, I_{CCD} <1.4 mA/MHz.

Note 4: Guaranteed, but not tested.

AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
f_{max}	Max Clock Frequency	200		200		MHz
t_{PLH} t_{PHL}	Propagation Delay $CPAB_n$ or $CPBA_n$ to A_n or B_n	1.5 1.5	5.3 5.3	1.5 1.5	5.3 5.3	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OEAB}_n$ or $\overline{OEBA}_n$ to A_n or B_n	1.5 1.5	5.5 5.5	1.5 1.5	5.5 5.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OEAB}_n$ or $\overline{OEBA}_n$ to A_n or B_n	1.5 1.5	6.0 6.0	1.5 1.5	6.0 6.0	ns

AC Operating Requirements

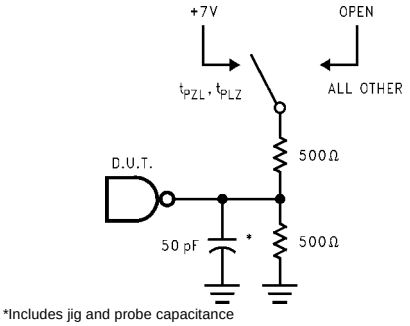
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW A_n or B_n to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	2.5 2.5		2.5 2.5		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW A_n or B_n to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	1.5 1.5		1.5 1.5		ns
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW $\overline{CEA}_n$ or $\overline{CEB}_n$ to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	2.5 2.5		2.5 2.5		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW $\overline{CEA}_n$ or $\overline{CEB}_n$ to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	1.5 1.5		1.5 1.5		ns
$t_W(H)$ $t_W(L)$	Pulse Width, HIGH or LOW to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	3.0 3.0		3.0 3.0		ns

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$ (Non I/O Pins)
$C_{I/O}$ (Note 5)	Output Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 5: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

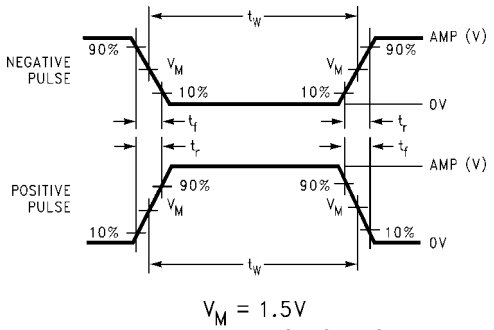


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Input Signal Requirements

AC Waveforms

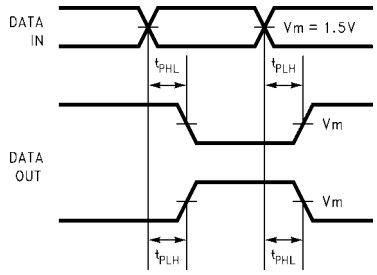


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

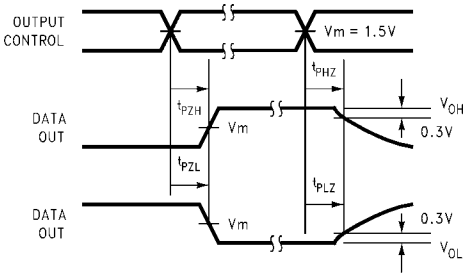


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

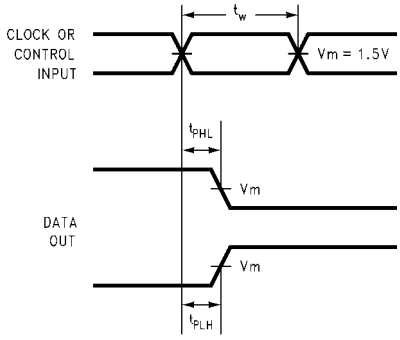


FIGURE 5. Propagation Delay, Pulse Width Waveforms

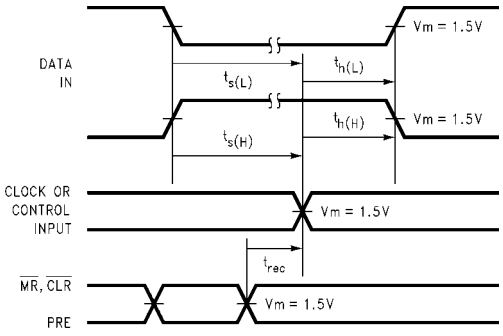
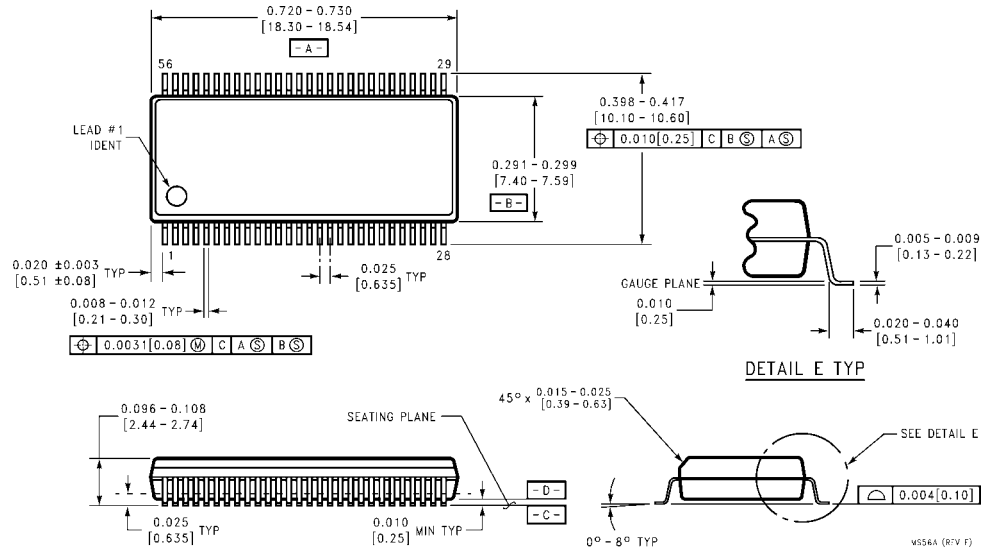


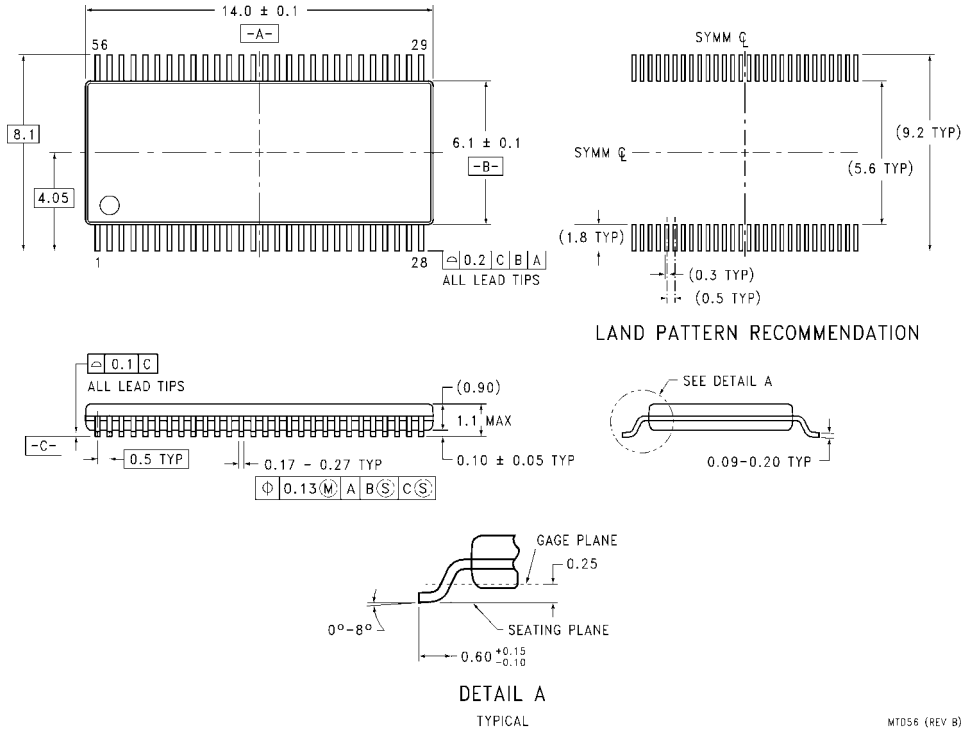
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

September 1996

74ABT16952
16-Bit Registered Transceiver with TRI-STATE® Outputs

General Description

The 'ABT16952 is a 16-bit registered transceiver. Two 8-bit back to back registers store data flowing in both directions between two bidirectional buses. Separate clock, clock enable and TRI-STATE® output enable signals are provided for each register. The output pins are guaranteed to source 32 mA (24 mA mil.) and to sink 64 mA (48 mA mil).

Features

- Separate clock, clock enable and TRI-STATE output enable provided for each register
- A and B output sink capability of 64 mA source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Commercial	Package Number	Package Description
74ABT16952CSSC (Note 1)	MS56A	56-Lead (0.300″ Wide) Molded Shrink Small Outline, JEDEC (SSOP)
74ABT16952CMTD (Notes 1, 2)	MTD56	56-Lead Molded Thin Shrink Small Outline, JEDEC (TSSOP)

Note 1: Devices also available in 13″ reel. Use suffix = SSCX and MTDX.

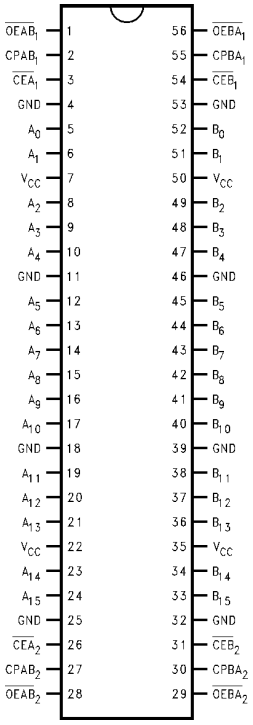
Note 2: Contact factory for package availability.

Pin Descriptions

Pin Names	Description
A_0–A_{16}	Data Register A Inputs/ B-Register TRI-STATE Outputs
B_0–B_{16}	Data Register B Inputs/ A-Register TRI-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
$\overline{CEA}_n$, $\overline{CEB}_n$	Clock Enable
$\overline{OEAB}_n$, $\overline{OEBA}_n$	Output Enable Inputs

Connection Diagram

Pin Assignment for SSOP



TL/F/11647–1

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Pin Descriptions (Continued)

Output Control

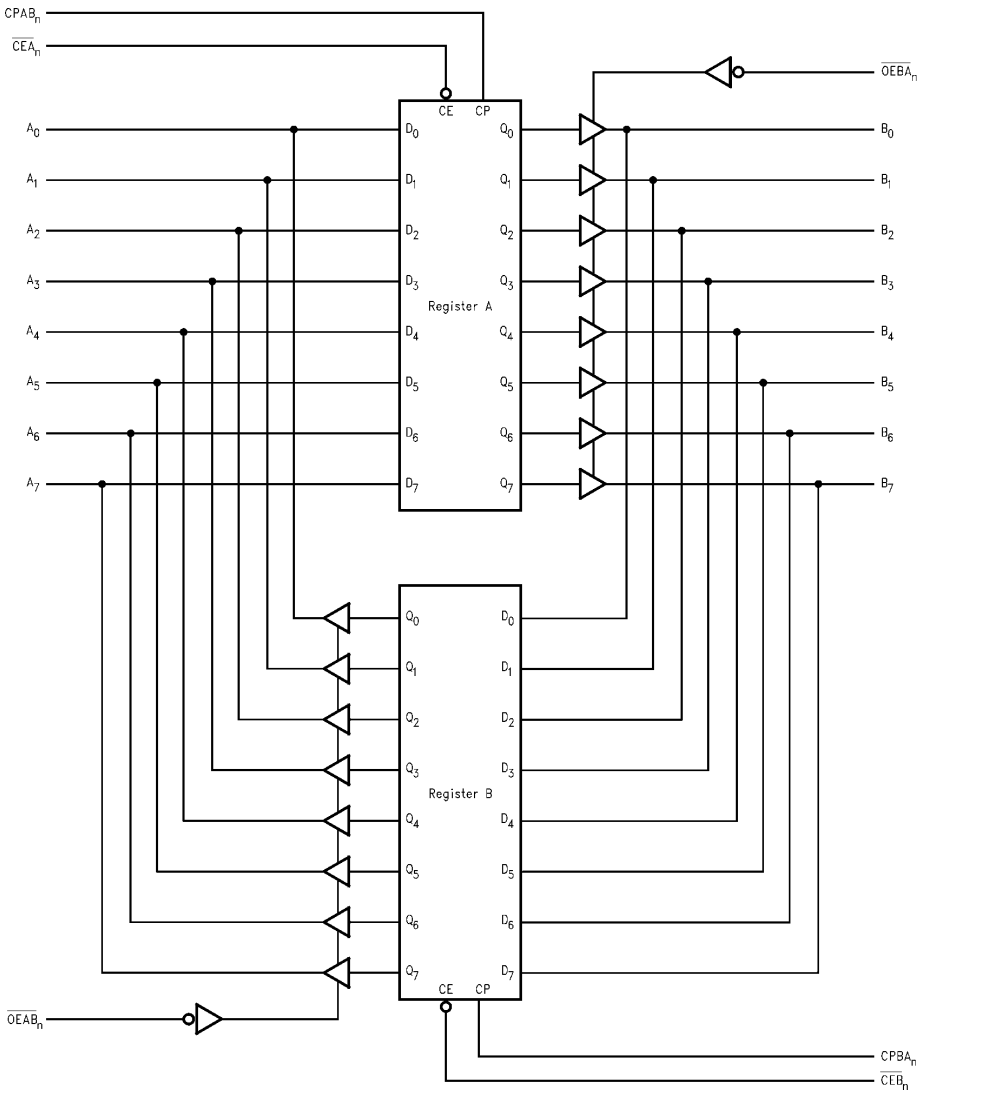
$\overline{OE}$	Internal Q	Output	Function
H	X	Z	Disable Outputs
L L	L H	L H	Enable Outputs

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance
↗ = LOW-to-HIGH Transition
NC = No Change

Register Function Table (Applies to A or B Register)

Inputs			Internal Q	Function
D	CP	$\overline{CE}$		
X	X	H	NC	Hold Data
L H	↗ ↗	L L	L H	Load Data

Block Diagram



TL/F/11647–2

n for either byte 1 or byte 2

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	−40°C to +85°C
Supply Voltage	
Commercial	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

DC Electrical Characteristics

Symbol	Parameter	ABT16952 Min	ABT16952 Typ	ABT16952 Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage 74ABT	2.5					I_{OH} = −3 mA (A_n, B_n)
	74ABT	2.0					I_{OH} = −32 mA (A_n, B_n)
V_{OL}	Output LOW Voltage 74ABT			0.55			I_{OL} = 64 mA (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 μA (Non-I/O Pins) All Other Pins Grounded
I_{IH}	Input HIGH Current			5	μA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 2) V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−5	μA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 2) V_{IN} = 0.0V (Non-I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			50	μA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OEA}$ or $\overline{OEB}$ = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current			−50	μA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OEA}$ or $\overline{OEB}$ = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	μA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	μA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			1.0	mA	Max	Outputs TRI-STATE; All Others GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V; All Others at V_{CC} or GND

DC Electrical Characteristics (Continued)

Symbol	Parameter	ABT16952			Units	V_{CC}	Conditions
		Min	Typ	Max			
I_{CCD}	Dynamic I_{CC} No Load (Note 2)			0.18	mA/MHz	Max	Outputs Open $\overline{OEA}$ or $\overline{OEB}$ = GND, Non-I/O = GND or V_{CC} One Bit toggling, 50% duty cycle (Note 1)

Note 1: For 8-bit toggling, $I_{CCD} < 1.4$ mA/MHz.

Note 2: Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	74ABT $T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		74ABT $T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V$ to $5.5V$ $C_L = 50$ pF		Units
		Min	Max	Min	Max	
f_{max}	Max Clock Frequency	200		200		MHz
t_{PLH} t_{PHL}	Propagation Delay $CPAB_n$ or $CPBA_n$ to A_n or B_n	1.5 1.5	5.3 5.3	1.5 1.5	5.3 5.3	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OEAB}_n$ or $\overline{OEBA}_n$ to A_n or B_n	1.5 1.5	5.5 5.5	1.5 1.5	5.5 5.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OEAB}_n$ or $\overline{OEBA}_n$ to A_n or B_n	1.5 1.5	6.0 6.0	1.5 1.5	6.0 6.0	ns

AC Operating Requirements

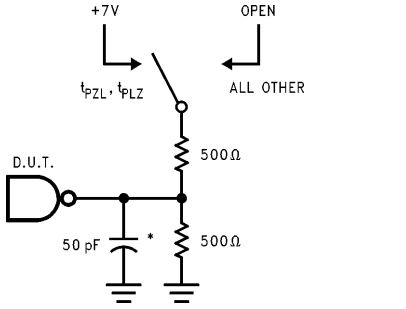
Symbol	Parameter	74ABT $T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		74ABT $T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V$ to $5.5V$ $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW A_n or B_n to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	2.5 2.5		2.5 2.5		ns
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW A_n or B_n to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	1.5 1.5		1.5 1.5		ns
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW $\overline{CEA}_n$ or $\overline{CEB}_n$ to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	2.5 2.5		2.5 2.5		ns
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW $\overline{CEA}_n$ or $\overline{CEB}_n$ to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	1.5 1.5		1.5 1.5		ns
$t_w(H)$ $t_w(L)$	Pulse Width, HIGH or LOW to $\overline{CPAB}_n$ or $\overline{CPBA}_n$	3.0 3.0		3.0 3.0		ns

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$ (Non I/O Pins)
$C_{I/O}$ (Note 1)	Output Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 1: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

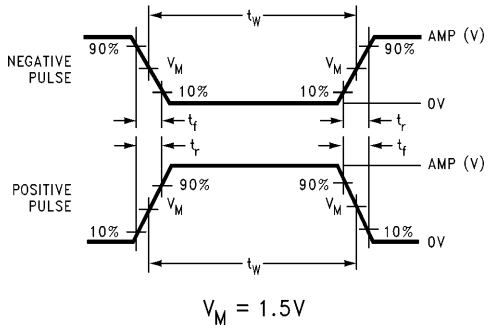
AC Loading



TL/F/11647–3

*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

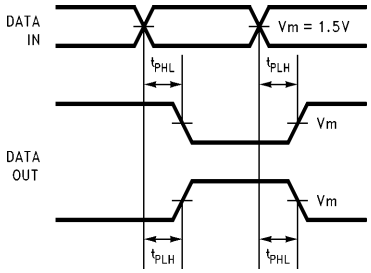


TL/F/11647–4

FIGURE 2a. Test Input Signal Levels

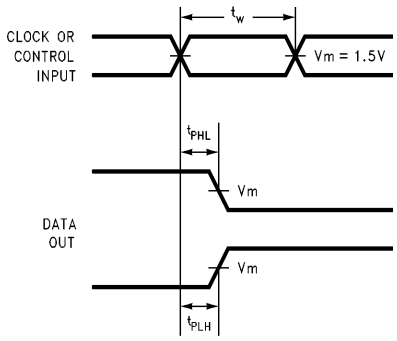
Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 2b. Input Signal Requirements



TL/F/11647–5

FIGURE 3. Propagation Delay Waveforms for Inverting and Non-Inveting Functions



TL/F/11647–6

FIGURE 4. Propagation Delay, Pulse Width Waveforms

AC Loading (Continued)

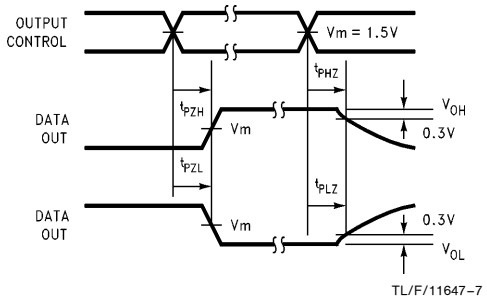


FIGURE 5. TRI-STATE Output HIGH and LOW Enable and Disable Times

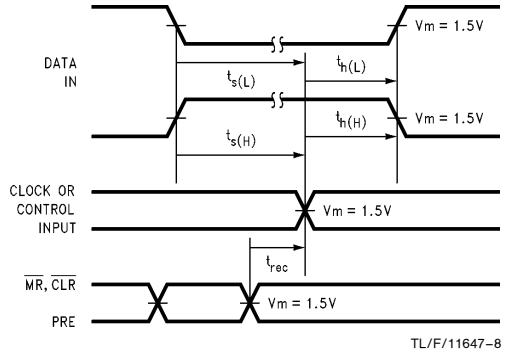
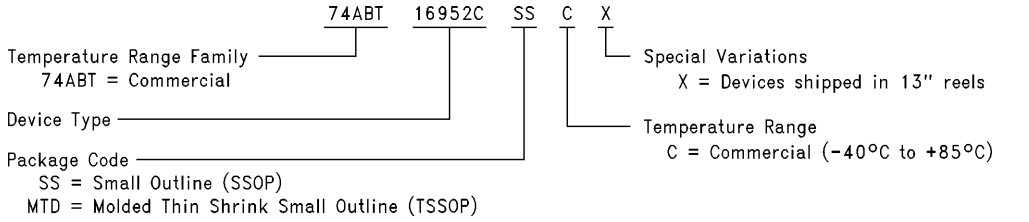


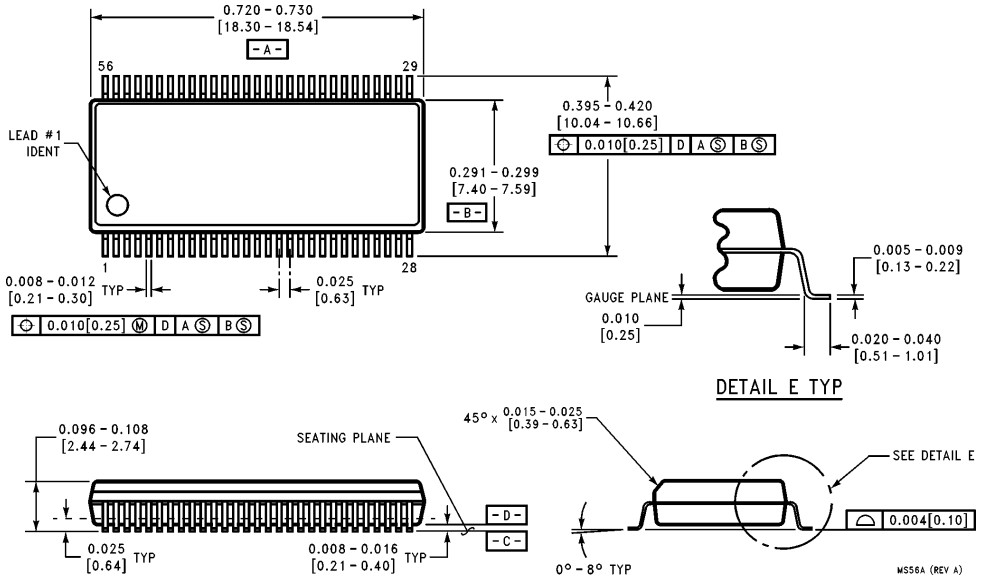
FIGURE 6. Setup Time, Hold Time and Recovery Time Waveforms

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

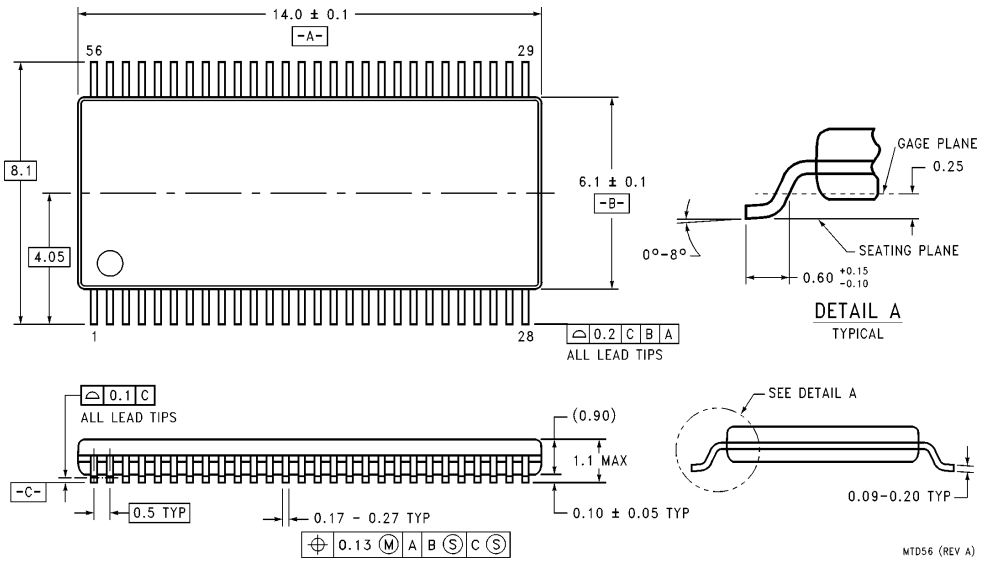


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead SSOP (0.300″ Wide) (SS)
74ABT16952CSSC or 74ABT16952CSSCX
NS Package Number MS56A

Physical Dimensions millimeters (Continued)



56-Lead Molded Thin Shrink Small Outline Package, JEDEC
74ABT16952CMTD
NS Package Number MTD56

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1994
Revised November 1999

74ABT2240
Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The ABT2240 is an inverting octal buffer and line driver designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers, and bus-oriented transmitters/receivers.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

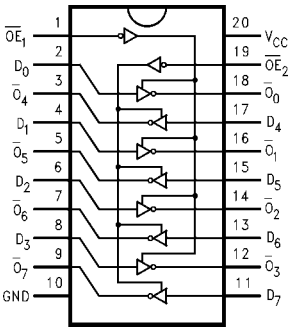
- Guaranteed latchup protection
- High impedance glitch-free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT2240CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT2240CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT2240CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT2240CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending letter suffix "X" to the ordering code.

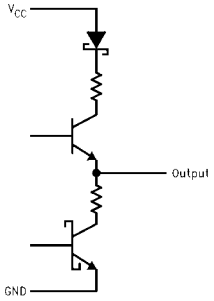
Connection Diagram



Pin Descriptions

Pin Names	Descriptions
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)
D_0–D_7	Data Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Schematic of Each Output



Truth Table

$\overline{OE}_1$	I_{0-3}	$\overline{O}_{0-3}$	$\overline{OE}_2$	I_{4-7}	$\overline{O}_{4-7}$
H	X	Z	H	X	Z
L	H	L	L	H	L
L	L	H	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	
(Across Comm Operating Range)	−300 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH		2.5			V	Min	I_{OH} = −3 mA
	Voltage		2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.8	V	Min	I_{OL} = 15 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test					V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}n$ = 2.0V
I_{OS}	Output Short-Circuit Current				−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}n$ = V_{CC} All Others at V_{CC}or GND
I_{CCT}	Additional	Outputs Enabled			1.5	mA	Max	V_I = V_{CC} − 2.1V
	I_{CC}/Input	Outputs 3-STATE			1.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC}or GND
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs OPEN
	(Note 3)				0.1	MHz		$\overline{OE}n$ = GND (Note 4)
								One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

AC Electrical Characteristics

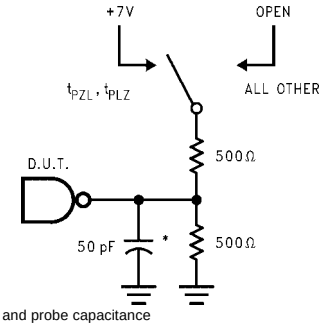
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	1.0		4.9	1.0	4.9	ns
t_{PHL}	Delay Data to Outputs	1.5		5.3	1.5	5.3	
t_{PZH}	Output Enable	1.5		6.6	1.5	6.6	ns
t_{PZL}	Time	2.7		6.9	2.7	6.9	
t_{PHZ}	Output Disable	1.9		6.4	1.9	6.4	ns
t_{PLZ}	Time	1.9		6.4	1.9	6.4	

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

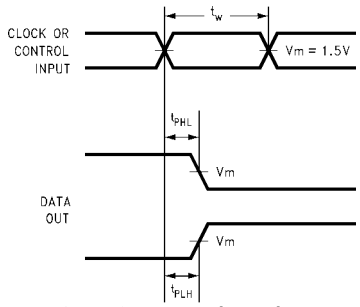


FIGURE 2. Propagation Delay, Pulse Width Waveforms

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

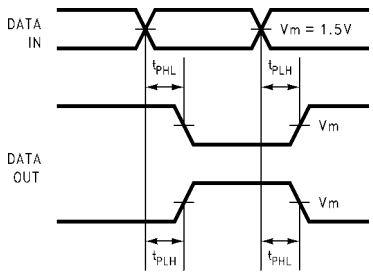


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

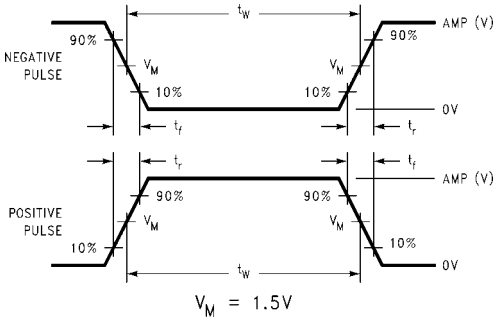


FIGURE 6. Test Input Signal Levels

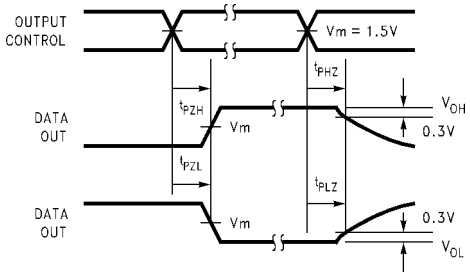


FIGURE 5. 3-STATE Output HIGH and LOW Enable and Disable Times

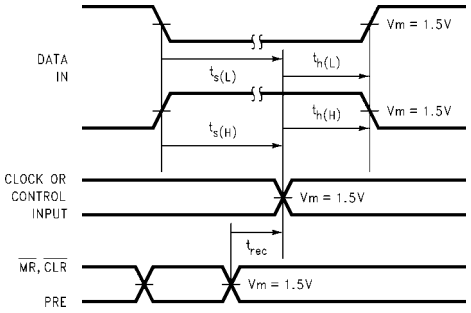
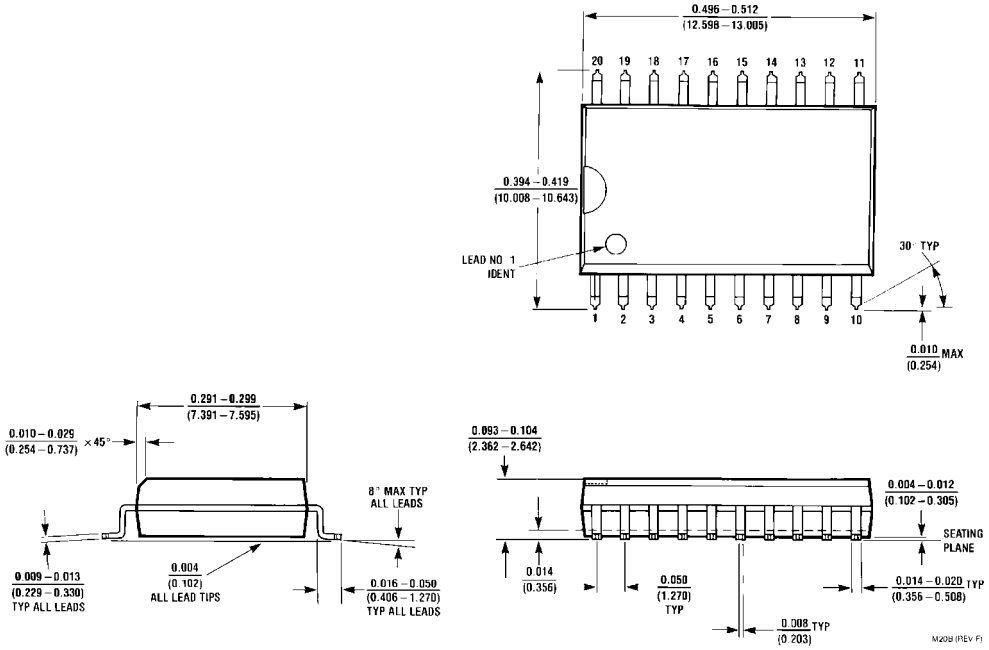


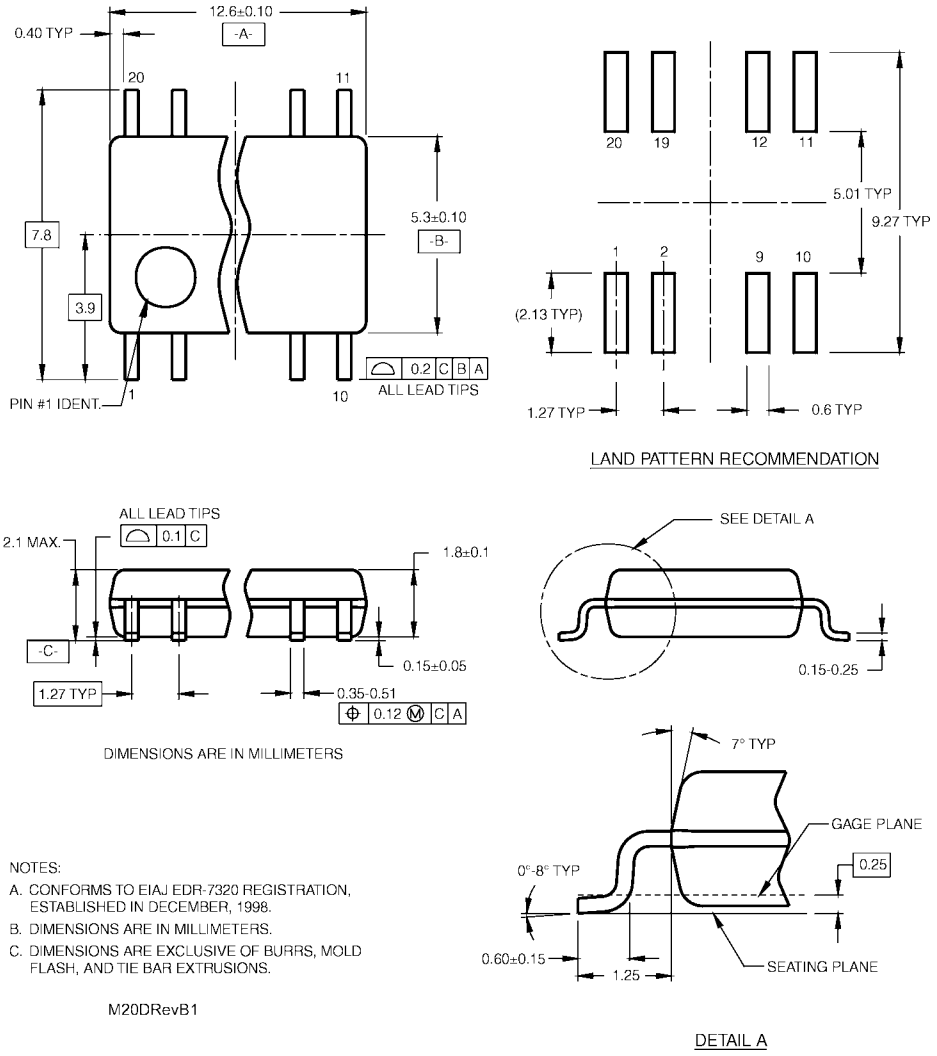
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

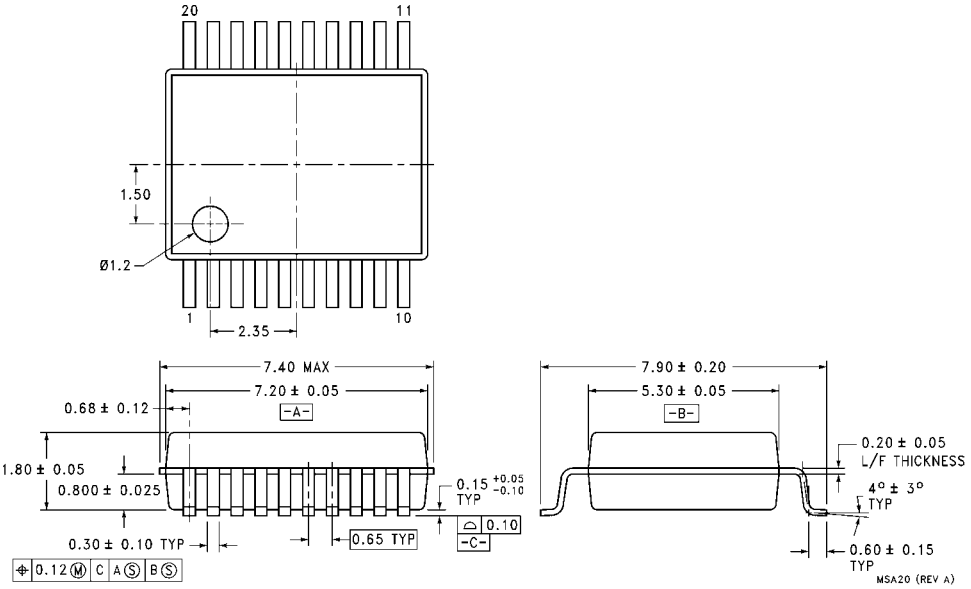
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

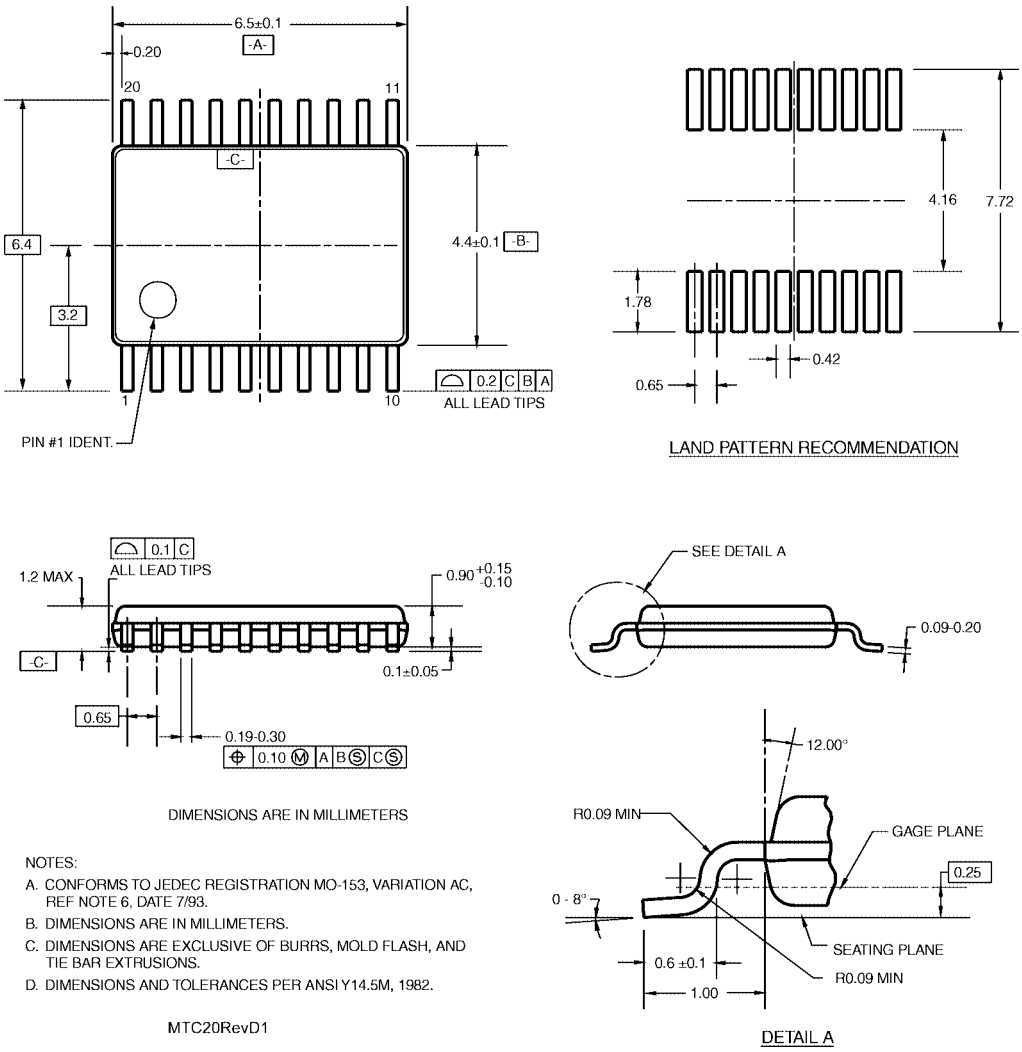
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1992
Revised November 1999

74ABT2244
Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The ABT2244 is an octal buffer and line driver designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers, and bus-oriented transmitters/receivers.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

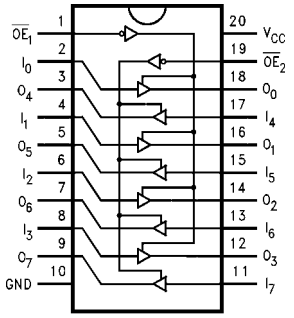
- Guaranteed latchup protection
- High impedance glitch-free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT2244CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT2244CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT2244CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT2244CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT2244CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices are also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

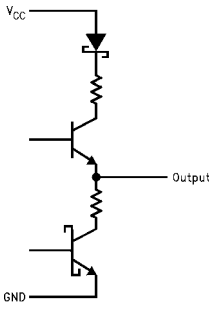
Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)
I_0–I_7	Inputs
O_0–O_7	Outputs

Schematic of Each Output



Truth Table

$\overline{OE}_1$	I_{0-3}	O_{0-3}	$\overline{OE}_2$	I_{4-7}	O_{4-7}
H	X	Z	H	X	Z
L	H	H	L	H	H
L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	
(Across Comm Operating Range)	−300 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.8	V	Min	I_{OL} = 15 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 4)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 4)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		475			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}$n = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}$n = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}$n = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional	Outputs Enabled			2.5	mA		V_I = V_{CC} − 2.1V
	I_{CC}/Input	Outputs 3-STATE			2.5	mA	Max	Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC}or GND
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs OPEN
	(Note 4)				0.1	MHz		$\overline{OE}$n = GND (Note 3)
								One Bit Toggling, 50% Duty Cycle

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

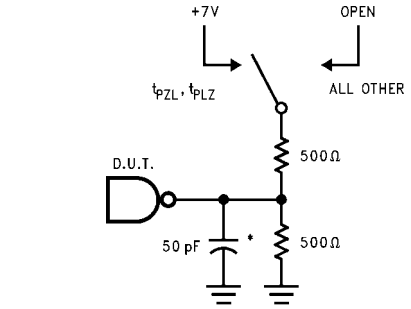
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	1.0	2.2	3.9	1.0	3.9	ns
t_{PHL}	Delay Data to Outputs	1.0	2.9	4.4	1.0	4.4	
t_{PZH}	Output Enable	1.5	3.7	6.0	1.5	6.0	ns
t_{PZL}	Time	2.1	4.3	7.0	2.1	7.0	
t_{PHZ}	Output Disable	1.7	3.5	5.8	1.7	5.8	ns
t_{PLZ}	Time	1.7	3.7	5.8	1.7	5.8	

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

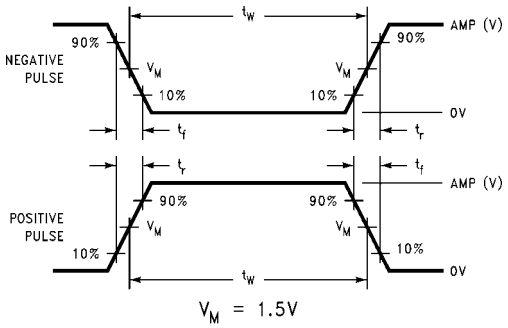


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_w	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

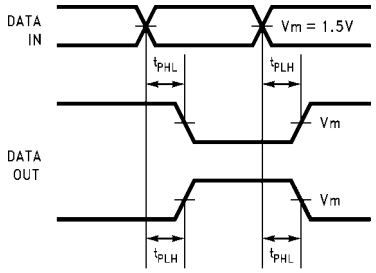


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

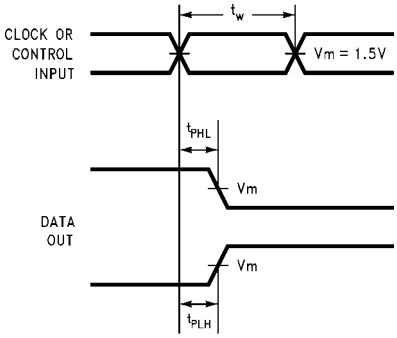


FIGURE 6. Propagation Delay, Pulse Width Waveforms

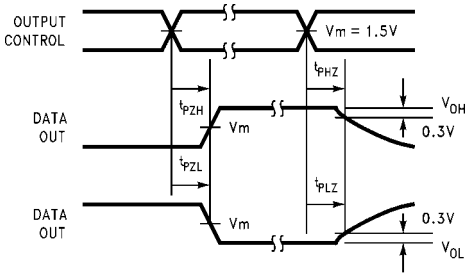


FIGURE 5. 3-STATE Output HIGH and LOW Enable and Disable Times

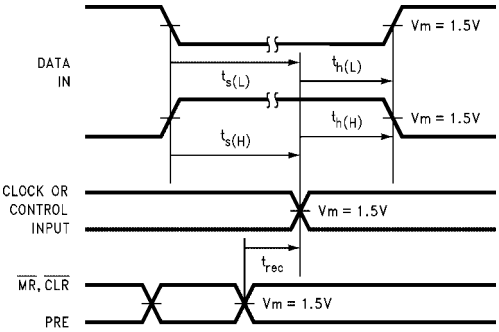
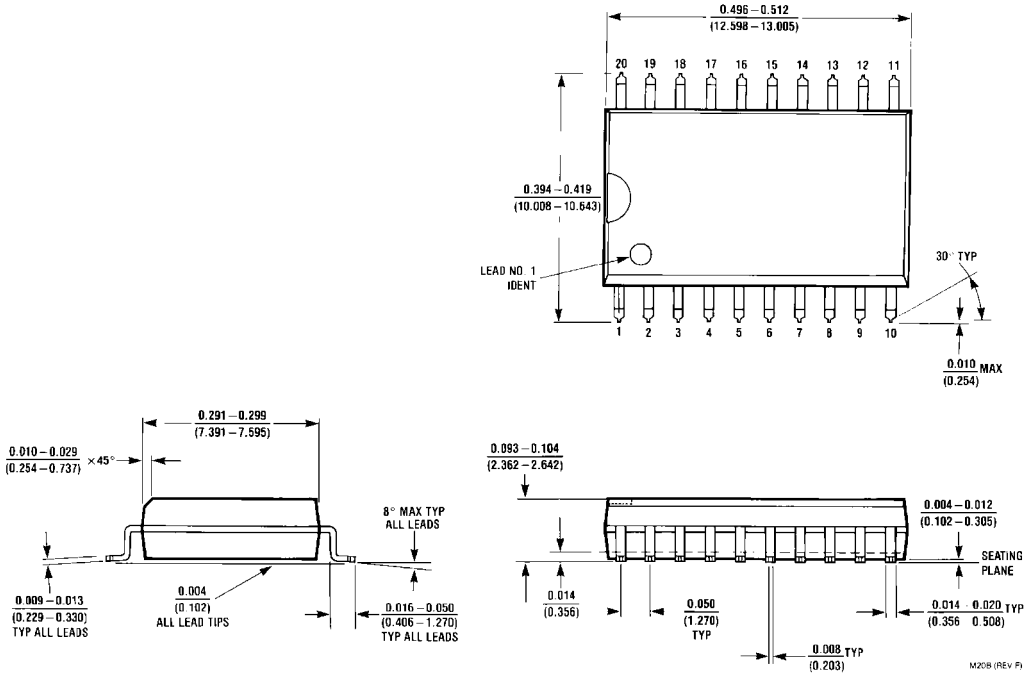


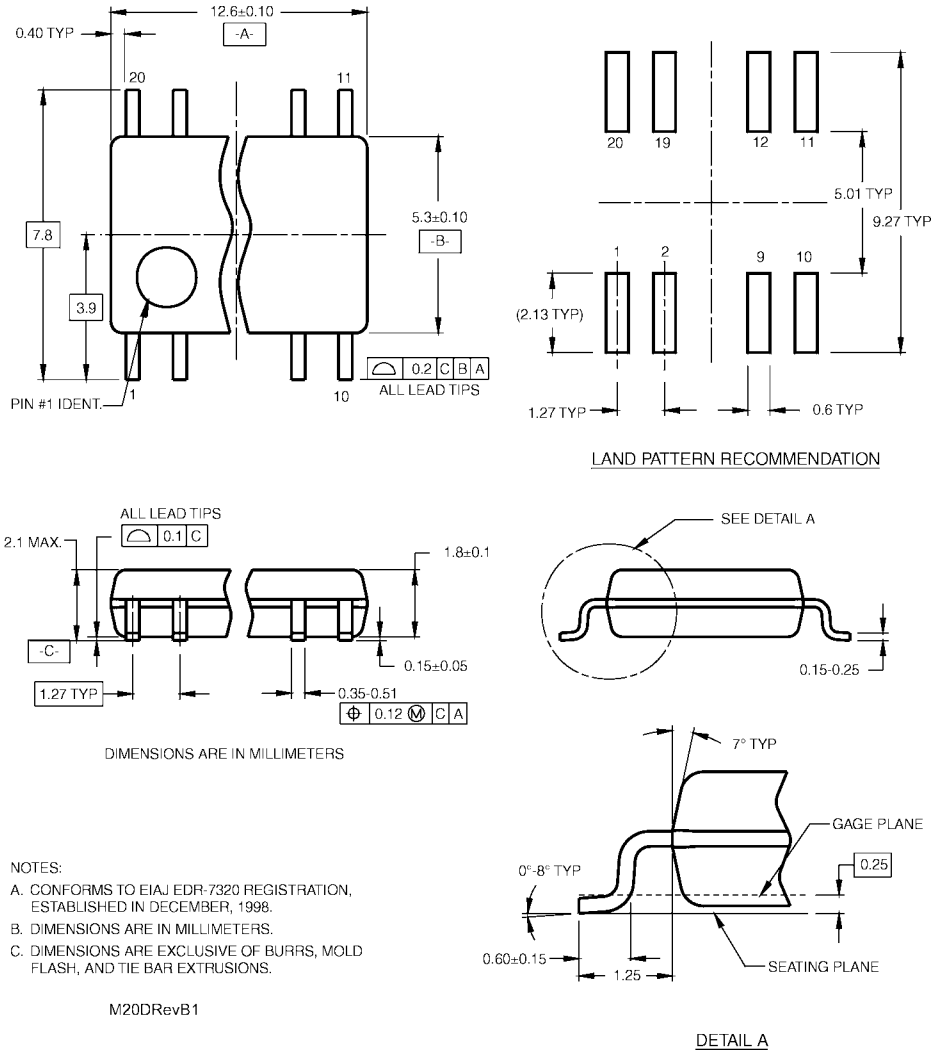
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

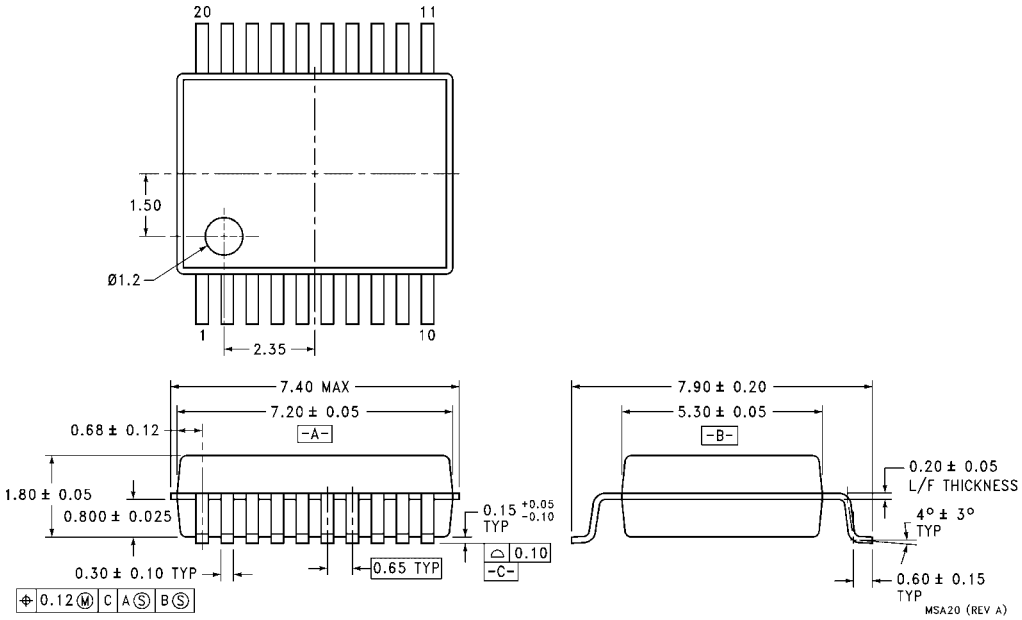
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

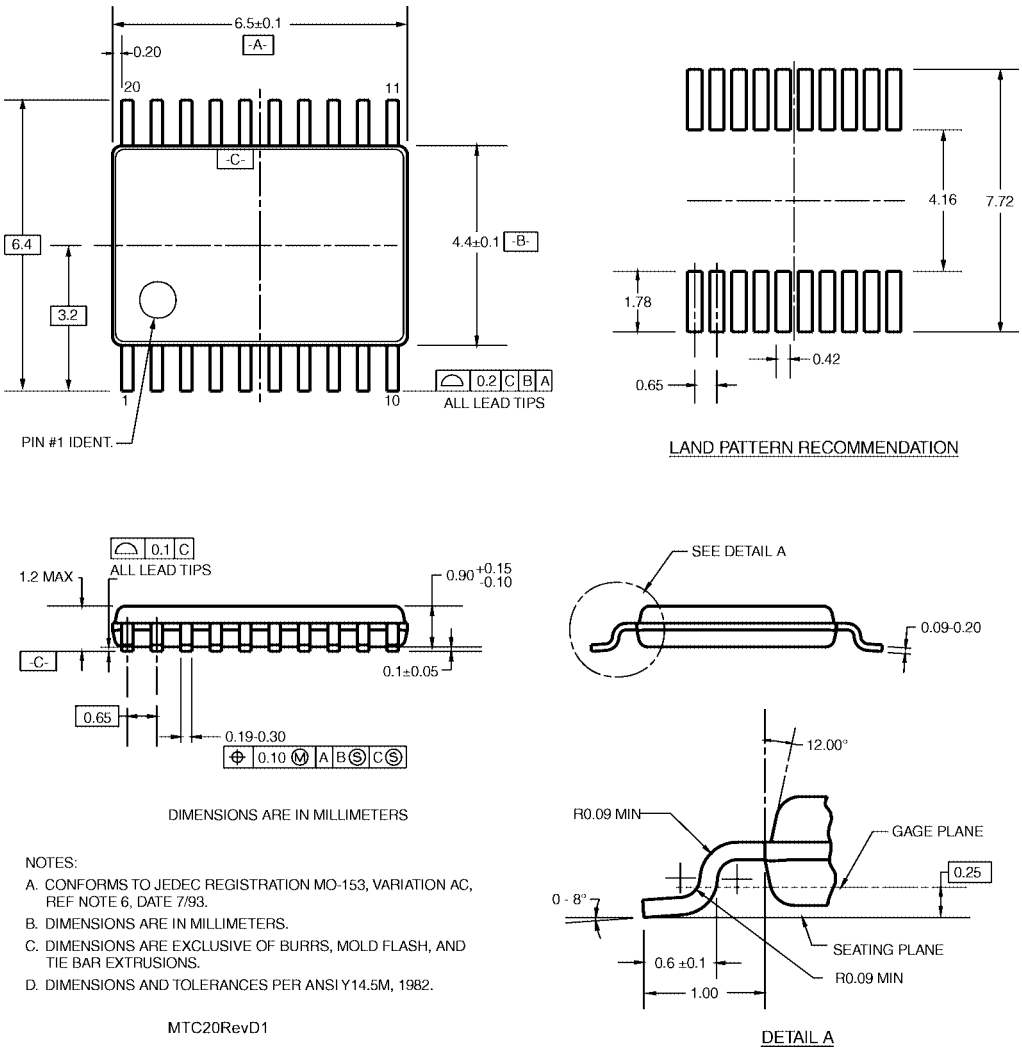
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

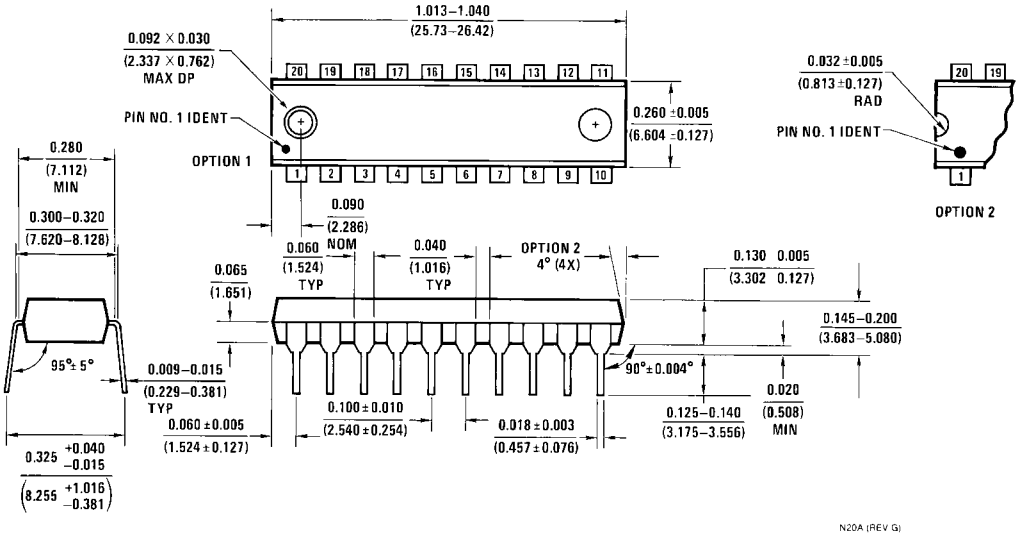
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1994
Revised November 1999

74ABT240
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

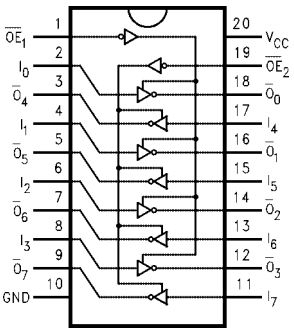
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT240CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT240CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT240CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT240CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	
(Across Comm Operating Range)	−150 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			1.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			1.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs Open
	(Note 3)				0.1	MHz		$\overline{OE}_n$ = GND, (Note 4)
								One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

AC Electrical Characteristics

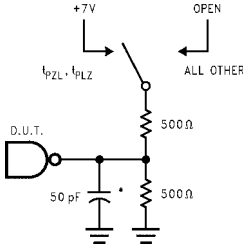
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0		4.8	0.8	5.5	1.0	4.8	ns
t_{PHL}	Data to Outputs	1.6		4.8	1.0	5.5	1.6	4.8	
t_{PZH}	Output Enable	1.1		6.2	0.8	7.5	1.1	6.2	ns
t_{PZL}	Time	1.1		6.2	0.8	7.7	1.1	6.2	
t_{PHZ}	Output Disable	1.8		6.4	1.0	7.5	1.8	6.4	ns
t_{PLZ}	Time	1.6		5.8	1.0	7.2	1.6	5.8	

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

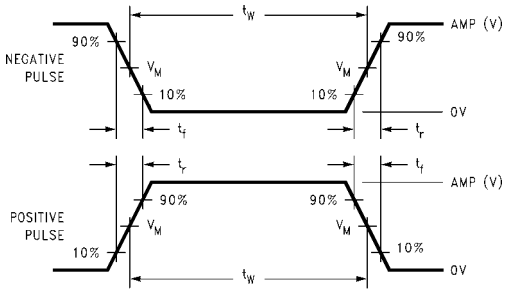
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

Standard AC Test Load



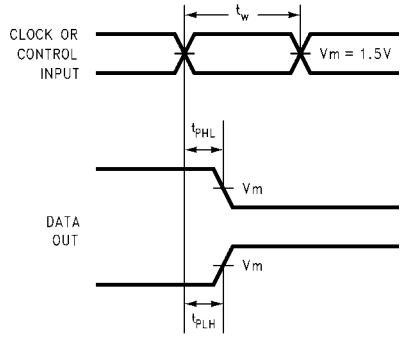
V_M = 1.5V

Test Input Signal Levels

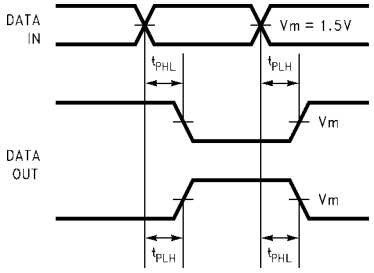
Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

Test Input Signal Requirements

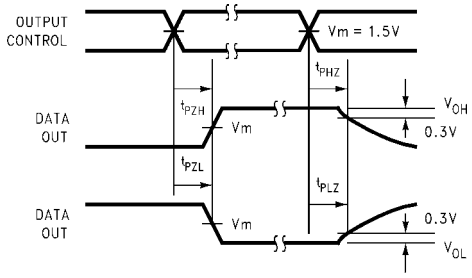
AC Waveforms



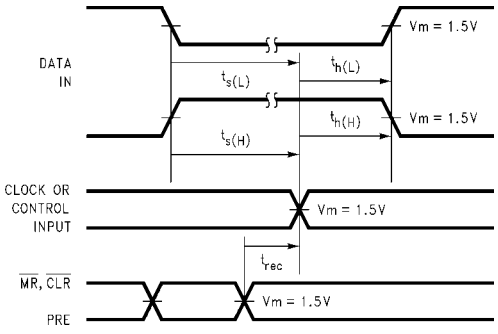
Propagation Delay,
Pulse Width Waveforms



Propagation Delay Waveforms for
Inverting and Non-Inverting Functions

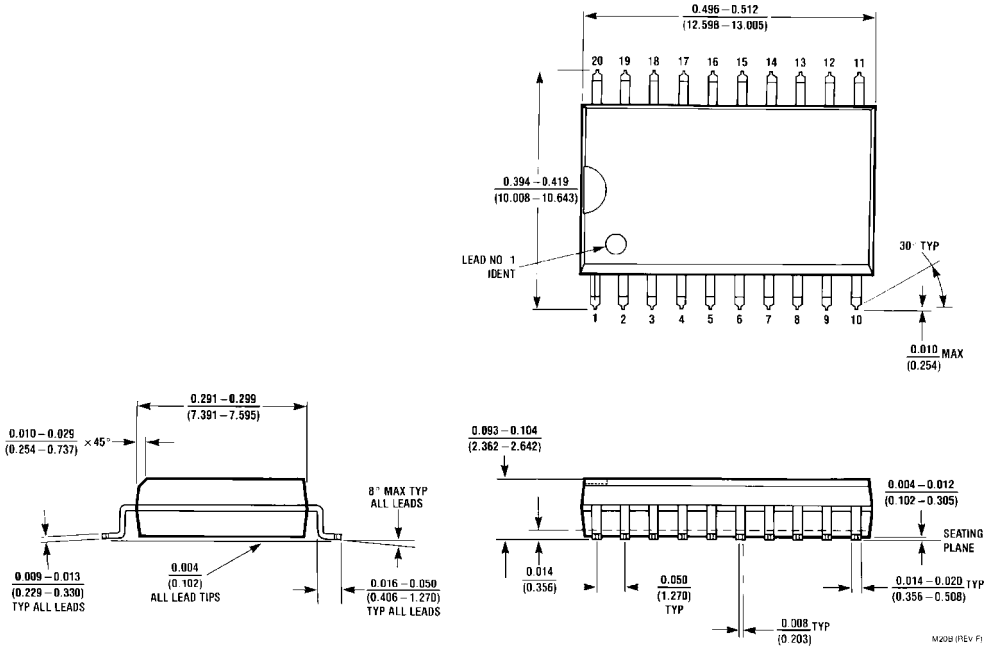


3-STATE Output HIGH
and LOW Enable and Disable Times



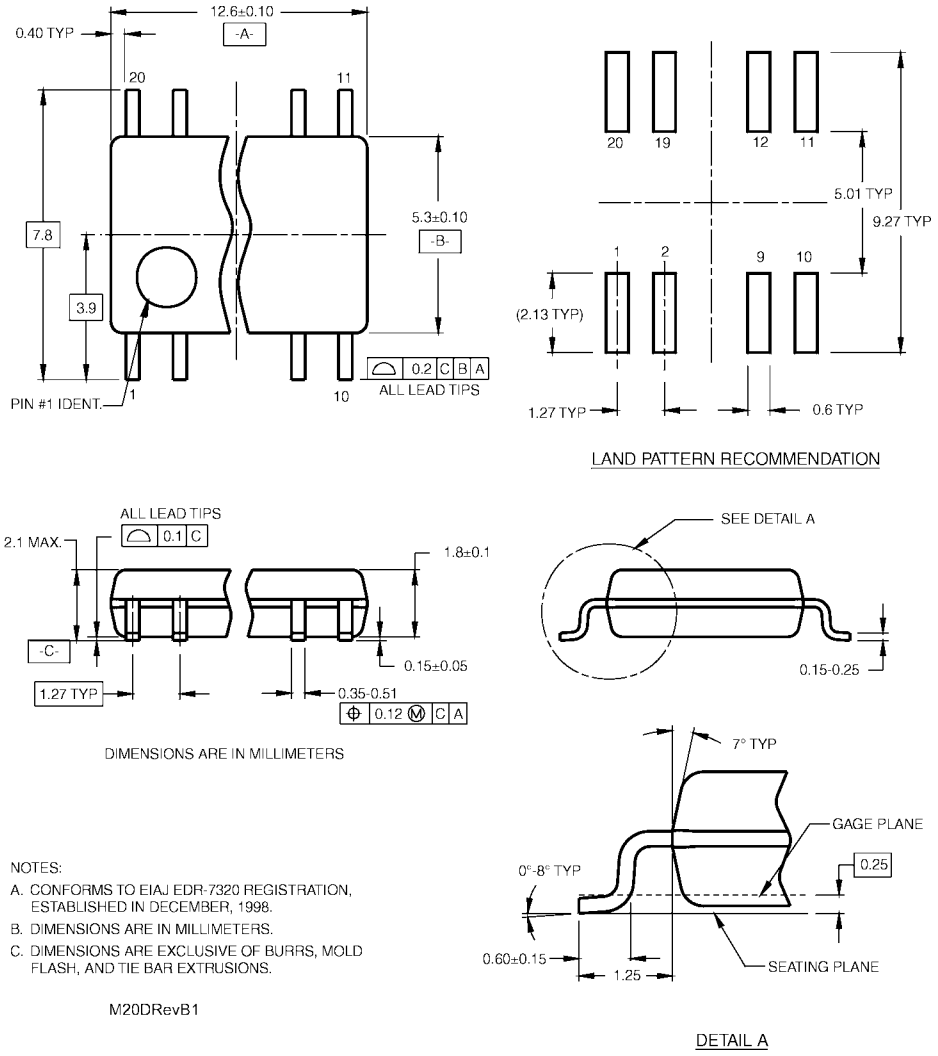
Setup Time, Hold Time
and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

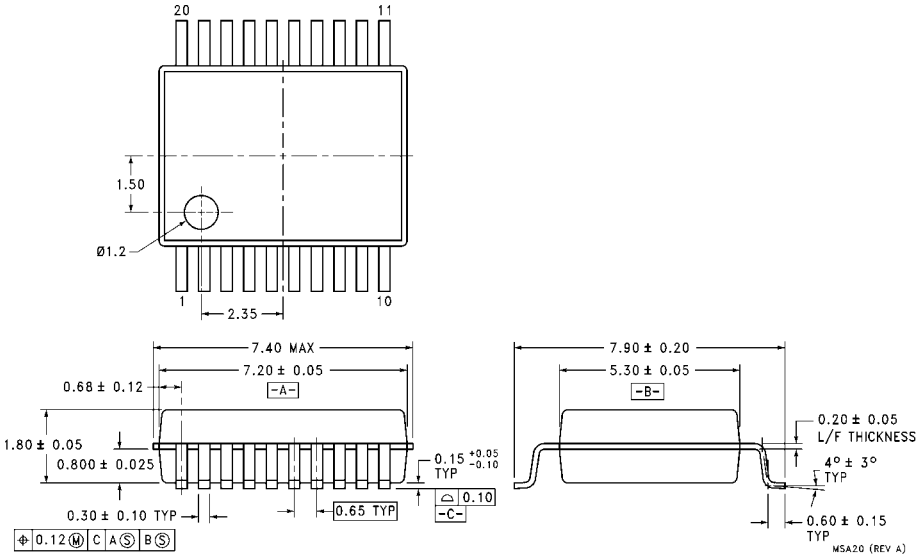
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

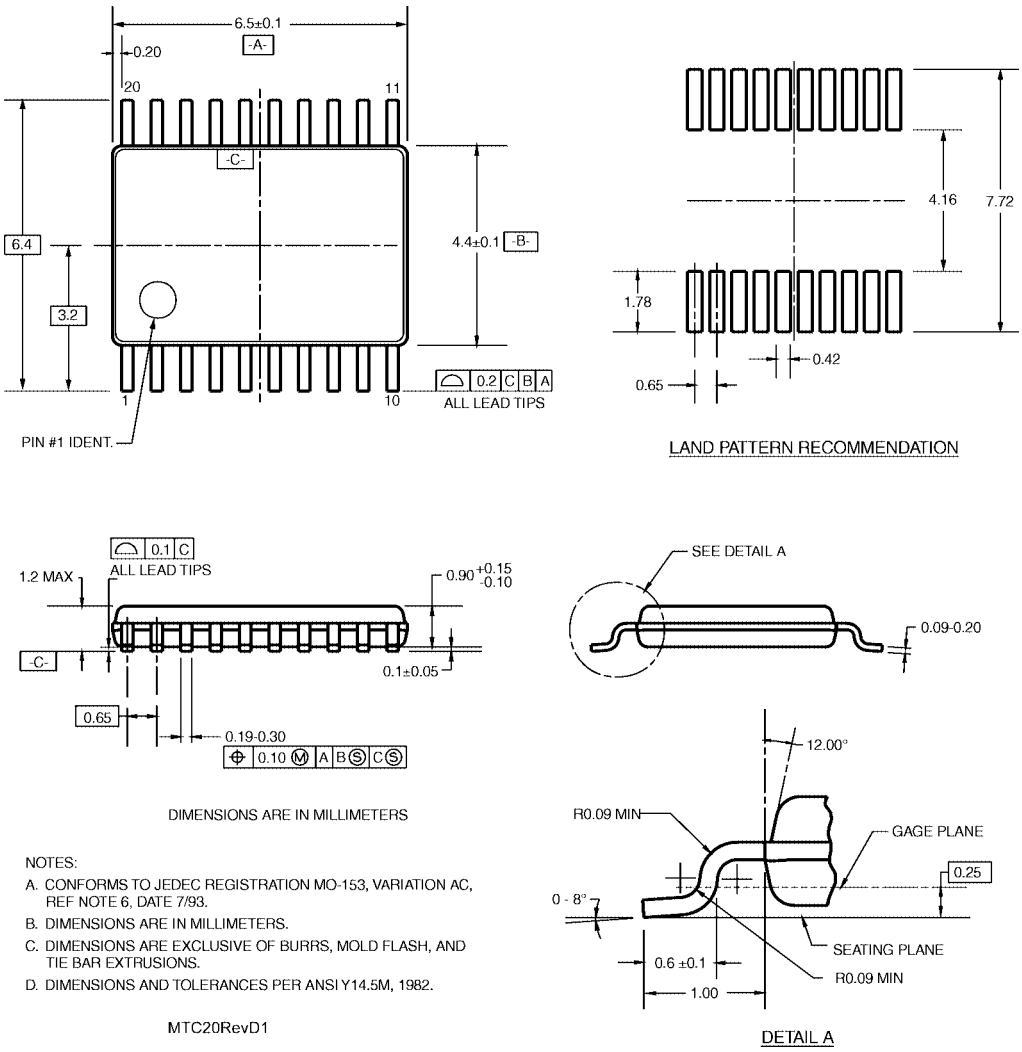
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1995
Revised November 1999

74ABT241
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT241 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver.

Features

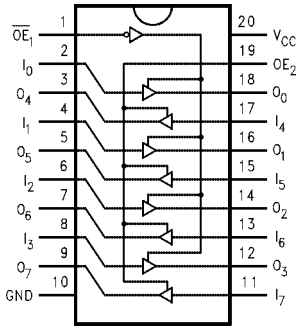
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT241CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT241CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT241CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT241CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$	Output Enable Input (Active LOW)
OE_2	Output Enable Input (Active HIGH)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Table

$\overline{OE}_1$	$I_{0–3}$	$O_{0–3}$	$\overline{OE}_2$	$I_{4–7}$	$O_{4–7}$
H	X	Z	L	X	Z
L	H	H	H	H	H
L	L	L	H	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	
(Over Comm Operating Range)	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 4)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 4)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs Open
	(Note 4)				0.1	MHz		$\overline{OE}_n$ = GND, (Note 3)
								One Bit Toggling, 50%
								Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.5	0.8	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.3	−0.8		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T_A = 25°C (Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.5		V	5.0	T_A = 25°C (Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.1	0.8	V	5.0	T_A = 25°C (Note 6)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP package)

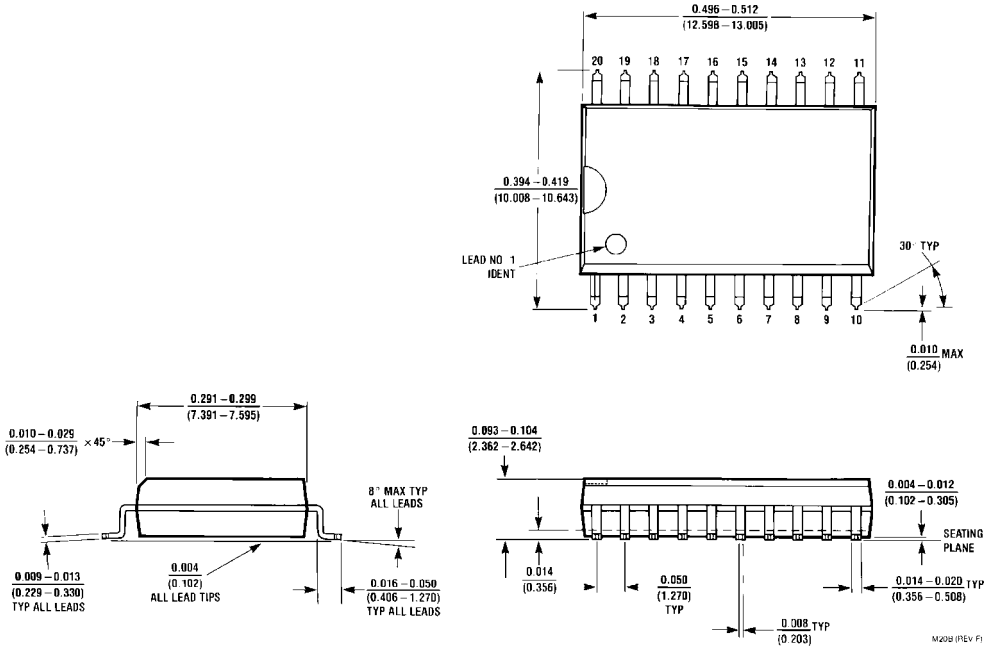
Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0		4.6	1.0	4.6	ns
t_{PHL}	Data to Outputs	1.0		4.6	1.0	4.6	
t_{PZH}	Output Enable	1.1		6.8	1.1	6.8	ns
t_{PZL}	Time	1.3		6.8	1.3	6.8	
t_{PHZ}	Output Disable	1.6		6.8	1.6	6.8	ns
t_{PLZ}	Time	1.0		5.9	1.0	5.9	

Capacitance

Symbol	Parameter	Typ	Units	Conditions T_A = 25°C
C_{IN}	Input Capacitance	5.0	pF	V_{CC} = 0V
C_{OUT} (Note 8)	Output Capacitance	9.0	pF	V_{CC} = 5.0V

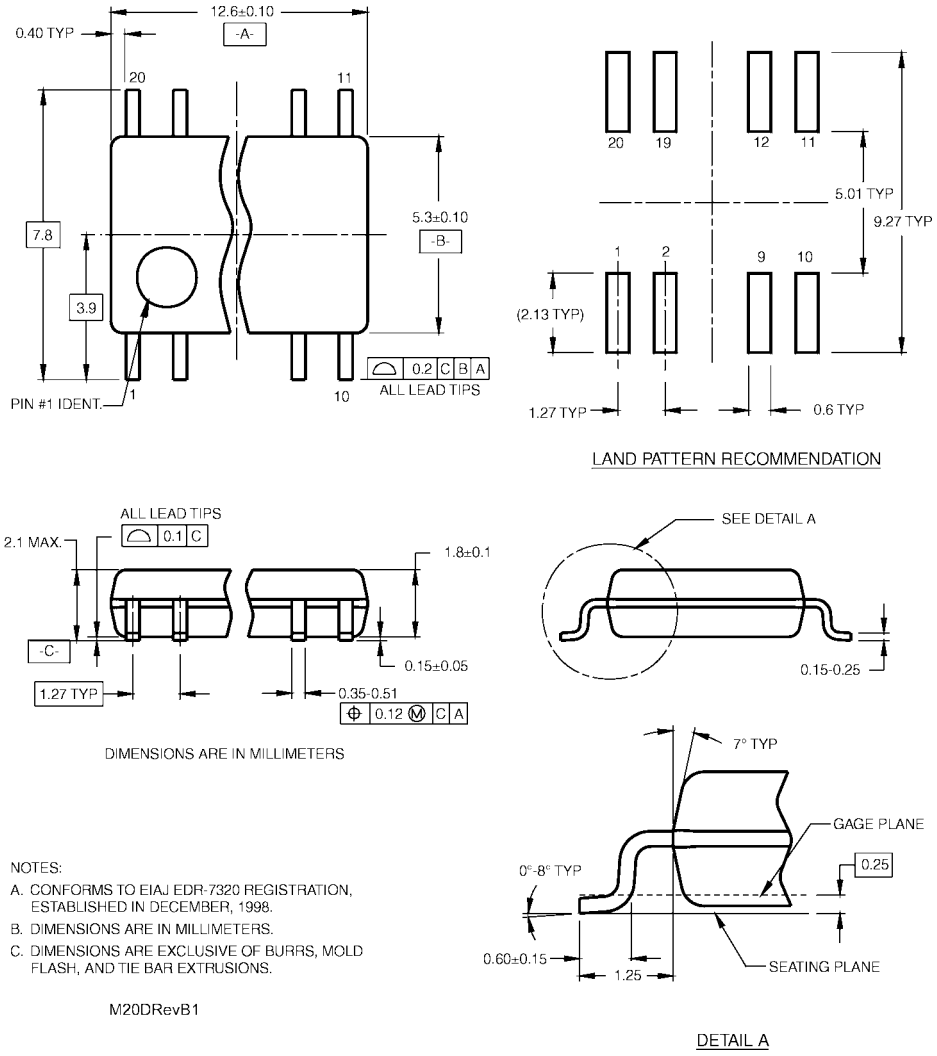
Note 8: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

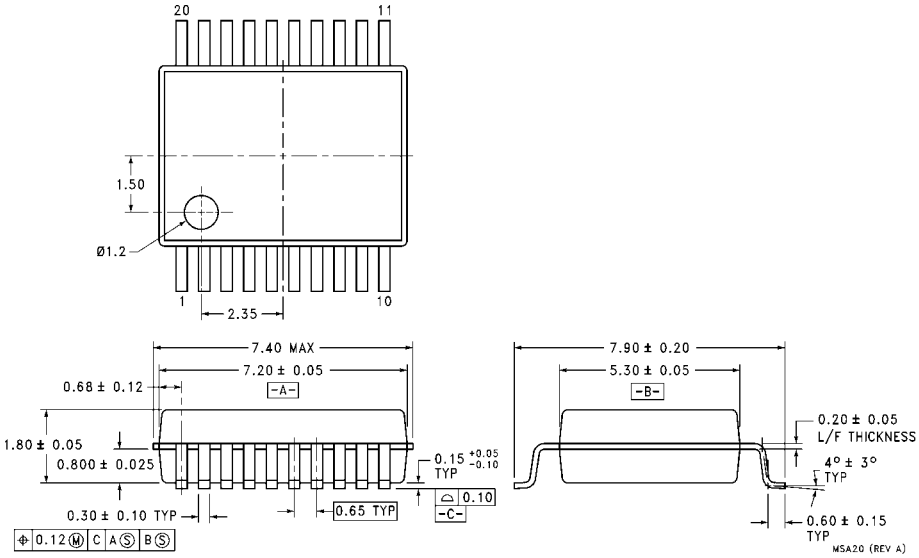
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

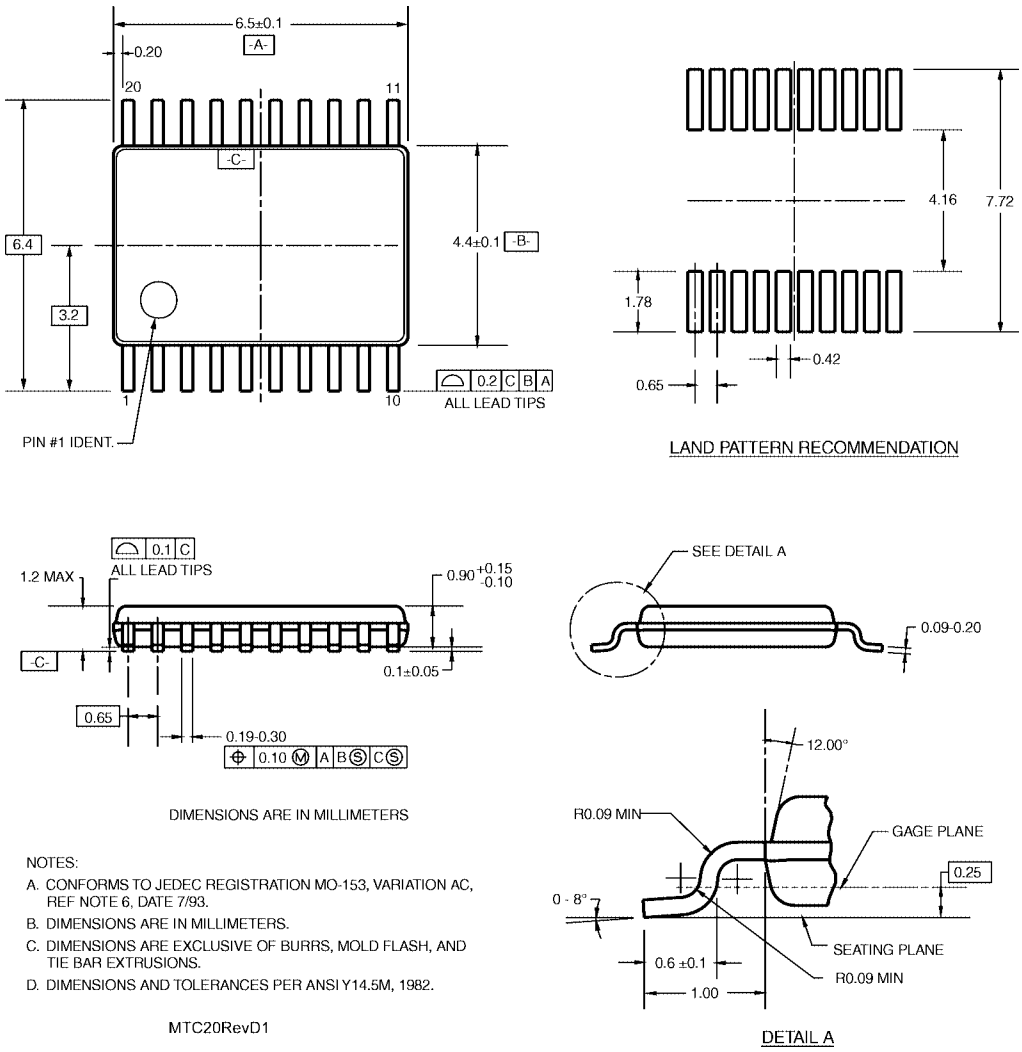
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

September 1995

74ABT241
Octal Buffer/Line Driver with TRI-STATE® Outputs

General Description

The 'ABT241 is an octal buffer and line driver with TRI-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver.

Features

- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

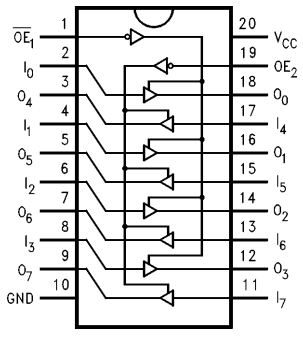
Commercial	Package Number	Package Description
74ABT241CSC (Note 1)	M20B	20-Lead (0.300″ Wide) Molded Small Outline, JEDEC
74ABT241CSJ (Note 1)	M20D	20-Lead (0.300″ Wide) Molded Small Outline, EIAJ
74ABT241CMSA (Note 1)	MSA20	20-Lead Molded Shrink Small Outline, EIAJ Type II
74ABT241CMTC (Notes 1, 2)	MTC20	20-Lead Molded Thin Shrink Small Outline, JEDEC

Note 1: Devices also available in 13″ reel. Use suffix = SCX, SJX, MSAX and MTCX.

Note 2: Contact factory for package availability.

Connection Diagram

Pin Assignment for DIP, SOIC and SSOP



TL/F/11691–1

Pin Names	Description
$\overline{OE}_1$	Output Enable Input (Active Low)
OE_2	Output Enable Input (Active High)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Table

$\overline{OE}_1$	I_{0-3}	O_{0-3}	$\overline{OE}_2$	I_{4-7}	O_{4-7}
H	X	Z	L	X	Z
L	H	H	H	H	H
L	L	L	H	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

 TL/F/11691 RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current (Over Comm Operating Range)	−500 mA
Over Voltage Latchup (I/O)	10V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	−40°C to +85°C
Supply Voltage	
Commercial	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns

DC Electrical Characteristics

Symbol	Parameter		ABT241 Min	ABT241 Typ	ABT241 Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	74ABT	2.5			V	Min	I_{OH} = −3 mA
		74ABT	2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage	74ABT			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				5 5	μA	Max	V_{IN} = 2.7V (Note 2) V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−5 −5	μA	Max	V_{IN} = 0.5V (Note 2) V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				50	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−50	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V Enable Input V_I = V_{CC} − 2.1V Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or Ground
		Outputs TRI-STATE			2.5	mA		
		Outputs TRI-STATE			50	μA		
I_{CCD}	Dynamic I_{CC} (Note 2)	No Load			0.1	mA/MHz	Max	Outputs Open $\overline{OE}_n$ = GND, (Note 1) One Bit Toggling, 50% Duty Cycle

Note 1: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.
Note 2: Guaranteed, but not tested.

DC Electrical Characteristics (SOIC package) (Continued)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.5	0.8	V	5.0	$T_A = 25°C$ (Note 1)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.3	−0.8		V	5.0	$T_A = 25°C$ (Note 1)
V_{OHV}	Minimum High Level Dynamic Output Voltage	2.7	3.1		V	5.0	$T_A = 25°C$ (Note 3)
V_{IHD}	Minimum High Level Dynamic Input Voltage	2.0	1.5		V	5.0	$T_A = 25°C$ (Note 2)
V_{ILD}	Maximum Low Level Dynamic Input Voltage		1.1	0.8	V	5.0	$T_A = 25°C$ (Note 2)

Note 1: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 2: Max number of data inputs (n) switching. n − 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 3: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics (SOIC and SSOP package)

Symbol	Parameter	74ABT $T_A = +25°C$, $V_{CC} = +5V$, $C_L = 50$ pF			74ABT $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0		4.6	1.0	4.6	ns
t_{PHL}	Data to Outputs	1.0		4.6	1.0	4.6	
t_{PZH}	Output Enable	1.1		6.8	1.1	6.8	ns
t_{PZL}	Time	1.3		6.8	1.3	6.8	
t_{PHZ}	Output Disable	1.6		6.8	1.6	6.8	ns
t_{PLZ}	Time	1.0		5.9	1.0	5.9	

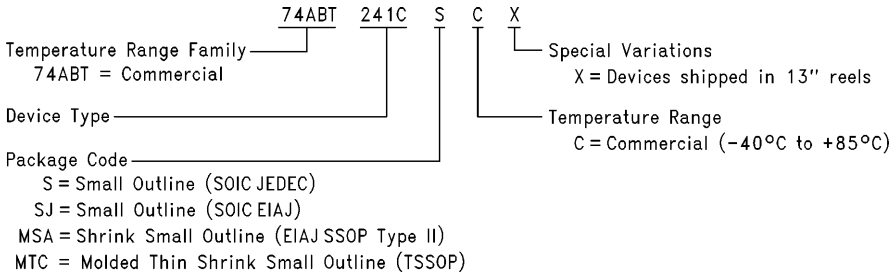
Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 1)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

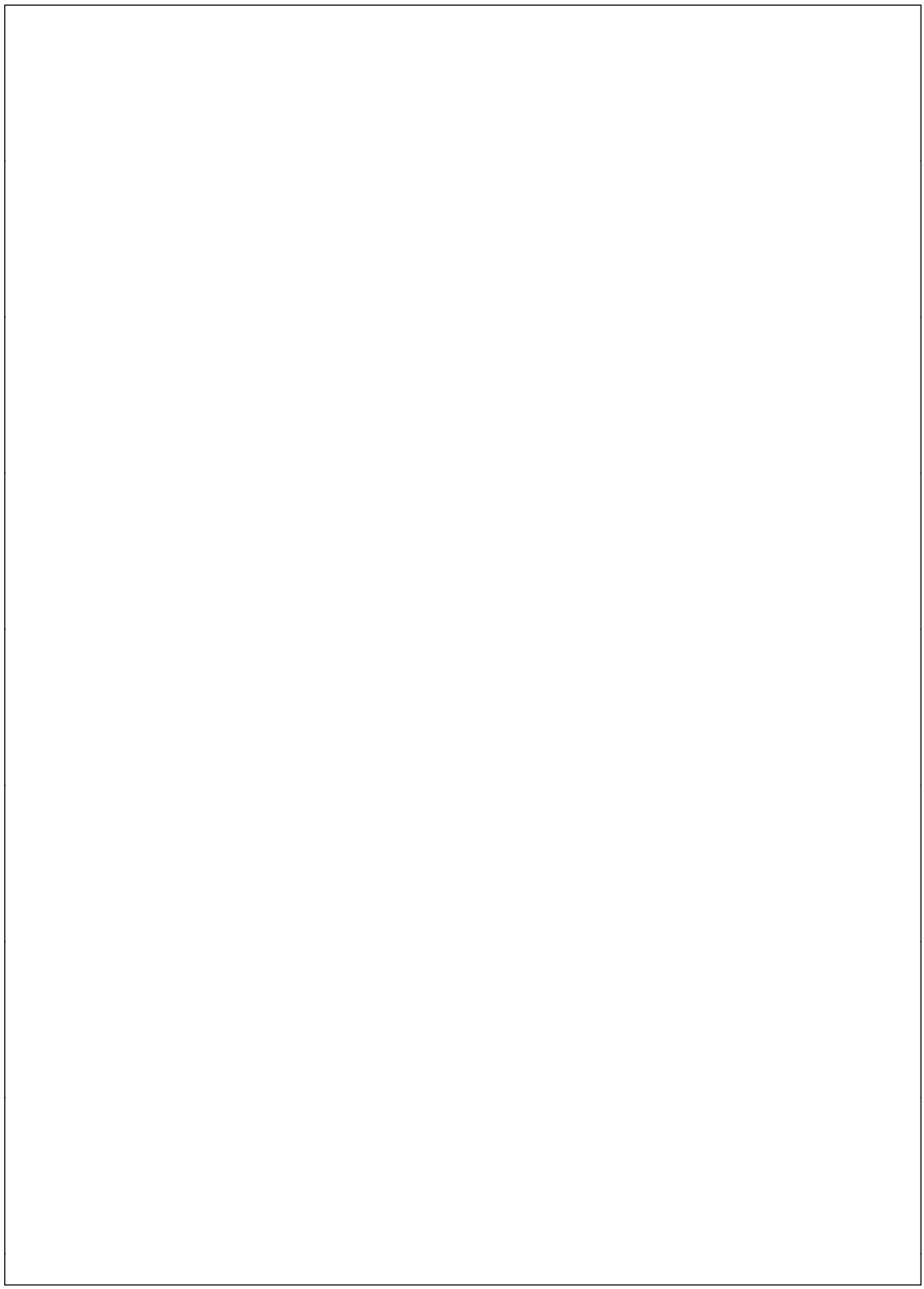
Note 1: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Ordering Information

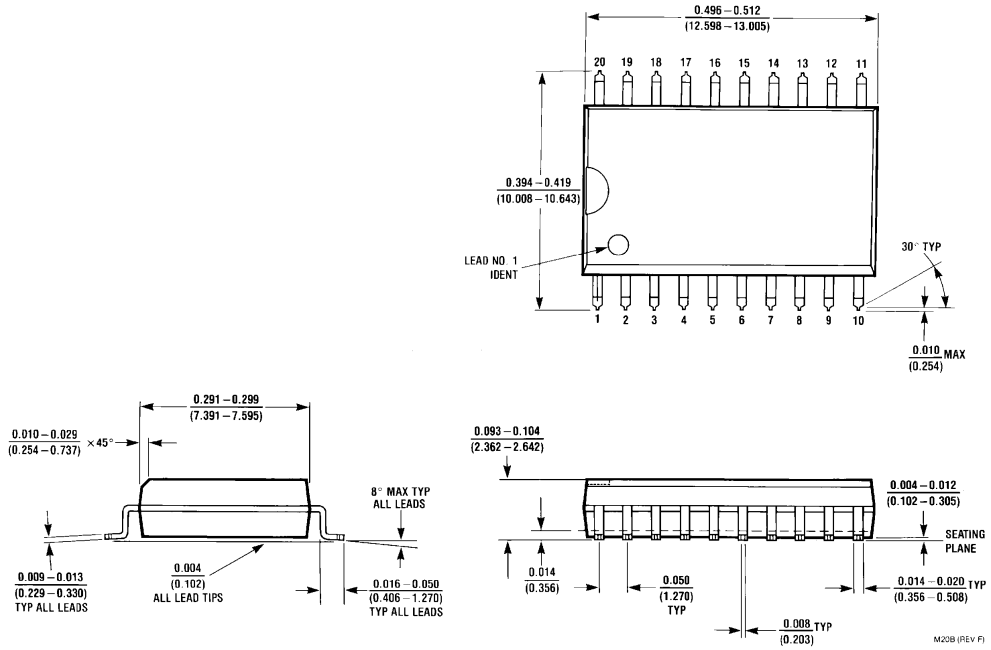
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



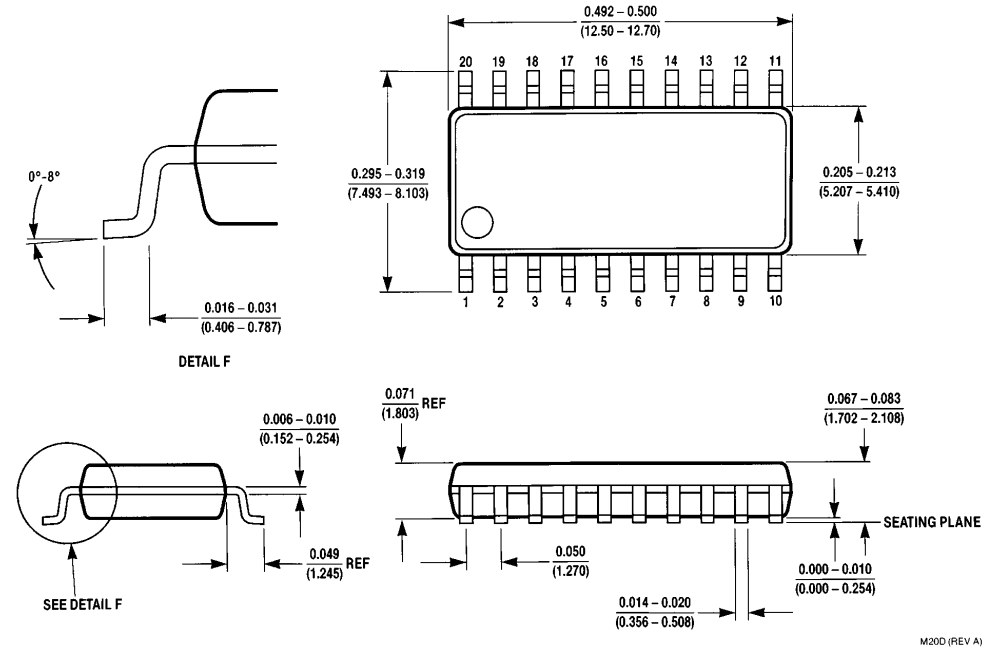
TL/F/11691–3



Physical Dimensions inches (millimeters)

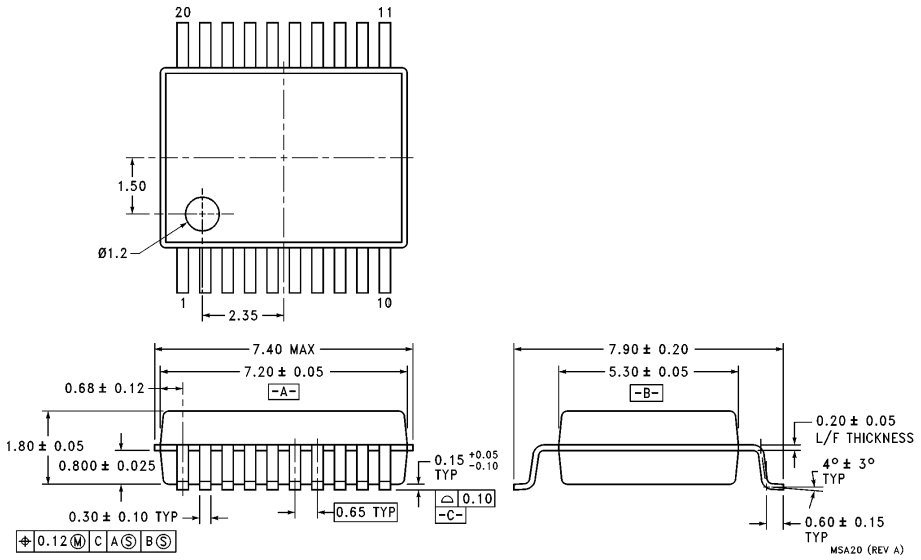


20-Lead Small Outline Integrated Circuit JEDEC (S)
NS Package Number M20B



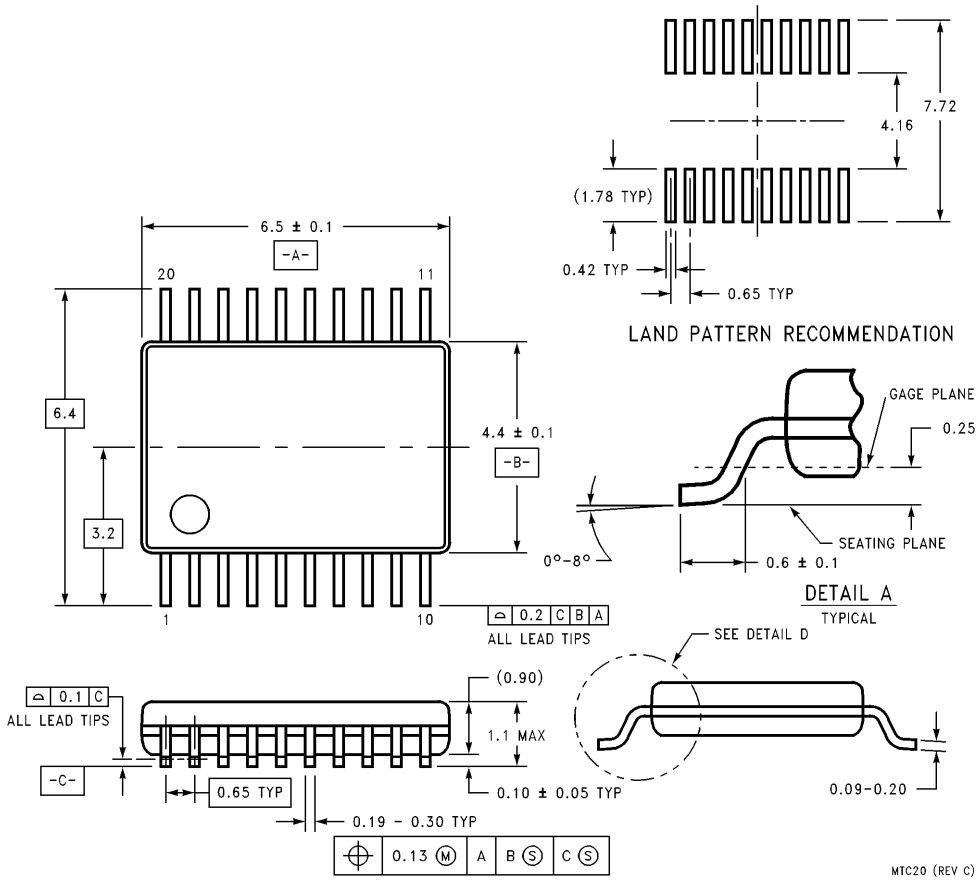
20-Lead Small Outline Integrated Circuit EIAJ (SJ)
NS Package Number M20D

Physical Dimensions millimeters (Continued)



20-Lead Plastic EIAJ SSOP (MSA)
NS Package Number MSA20

Physical Dimensions millimeters (Continued)



20-Lead Molded Thin Shrink Small Outline Package, JEDEC
NS Package Number MTC20

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1992
Revised November 1999

74ABT244
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT244 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver.

Features

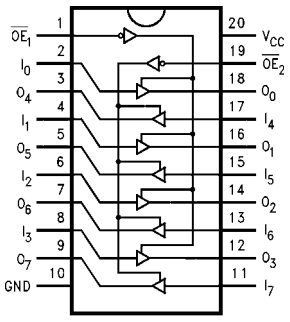
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT244CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT244CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT244CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT244CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT244CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Table

$\overline{OE}_1$	I_{0-3}	O_{0-3}	$\overline{OE}_2$	I_{4-7}	O_{4-7}
H	X	Z	H	X	Z
L	H	H	L	H	H
L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55			I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 4)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 4)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}, All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs OPEN
	(Note 4)				0.1	MHz		$\overline{OE}_n$ = GND, (Note 3)
								One Bit Toggling, 50% Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.5	0.8	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.3	–0.8		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T_A = 25°C (Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.5		V	5.0	T_A = 25°C (Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.1	0.8	V	5.0	T_A = 25°C (Note 6)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.5	3.6	1.0	5.3	1.0	3.6	ns
t_{PHL}	Data to Outputs	1.0	2.3	3.6	1.0	5.0	1.0	3.6	
t_{PZH}	Output Enable	1.5	3.5	6.0	0.8	6.5	1.5	6.0	ns
t_{PZL}	Time	1.5	3.6	6.0	1.2	7.9	1.5	6.0	
t_{PHZ}	Output Disable	1.7	3.5	5.6	1.2	7.6	1.7	5.6	ns
t_{PLZ}	Time	1.7	3.3	5.6	1.0	7.9	1.7	5.6	

Extended AC Electrical Characteristics

(SOIC package)

Symbol	Parameter	T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 8 Outputs Switching (Note 8)			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 9)		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 8 Outputs Switching (Note 10)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.5	ns
t_{PHL}	Data to Outputs	1.5		5.0	1.5	6.0	2.5	8.5	
t_{PZH}	Output Enable Time	1.5		6.5	2.5	7.5	2.5	10.0	ns
t_{PZL}		1.5		6.5	2.5	7.5	2.5	12.0	
t_{PHZ}	Output Disable Time	1.0		5.6	(Note 11)		(Note 11)		ns
t_{PLZ}		1.0		5.6					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 14) Max	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 15) Max	Units
t_{OSHL} (Note 12)	Pin to Pin Skew HL Transitions	0.8	1.8	ns
t_{OSLH} (Note 12)	Pin to Pin Skew LH Transitions	0.8	1.8	ns
t_{PS} (Note 16)	Duty Cycle LH–HL Skew	1.0	2.5	ns
t_{OST} (Note 12)	Pin to Pin Skew LH/HL Transitions	1.0	2.5	ns
t_{PV} (Note 13)	Device to Device Skew LH/HL Transitions	1.5	3.0	ns

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 13: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Note 14: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 15: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

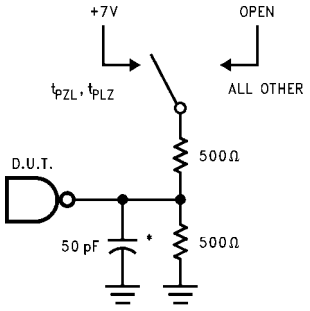
Note 16: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 17)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

AC Waveforms

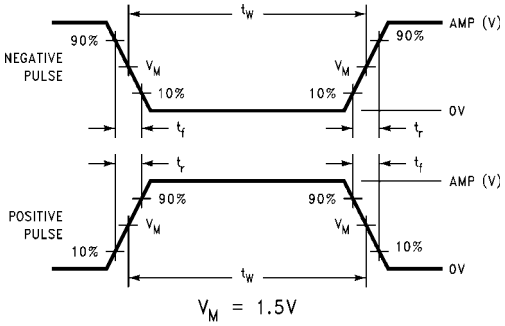


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

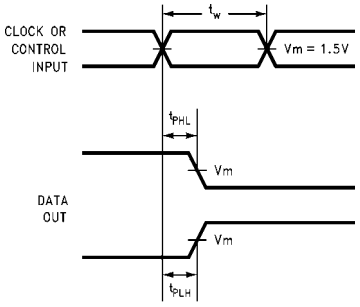


FIGURE 4. Propagation Delay, Pulse Width Waveforms

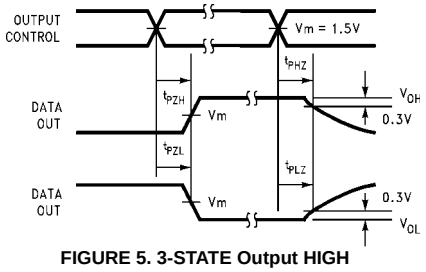


FIGURE 5. 3-STATE Output HIGH and LOW Enable and Disable Times

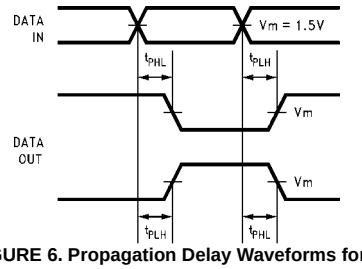


FIGURE 6. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

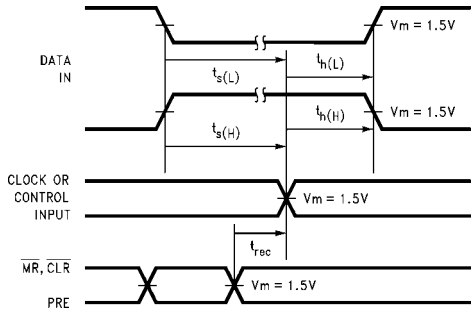
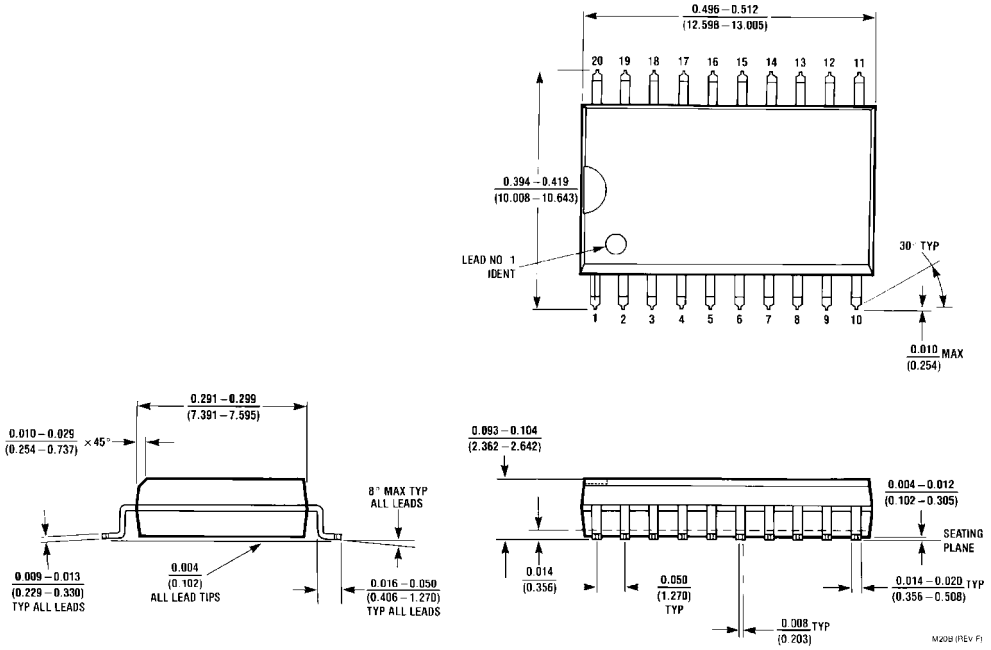


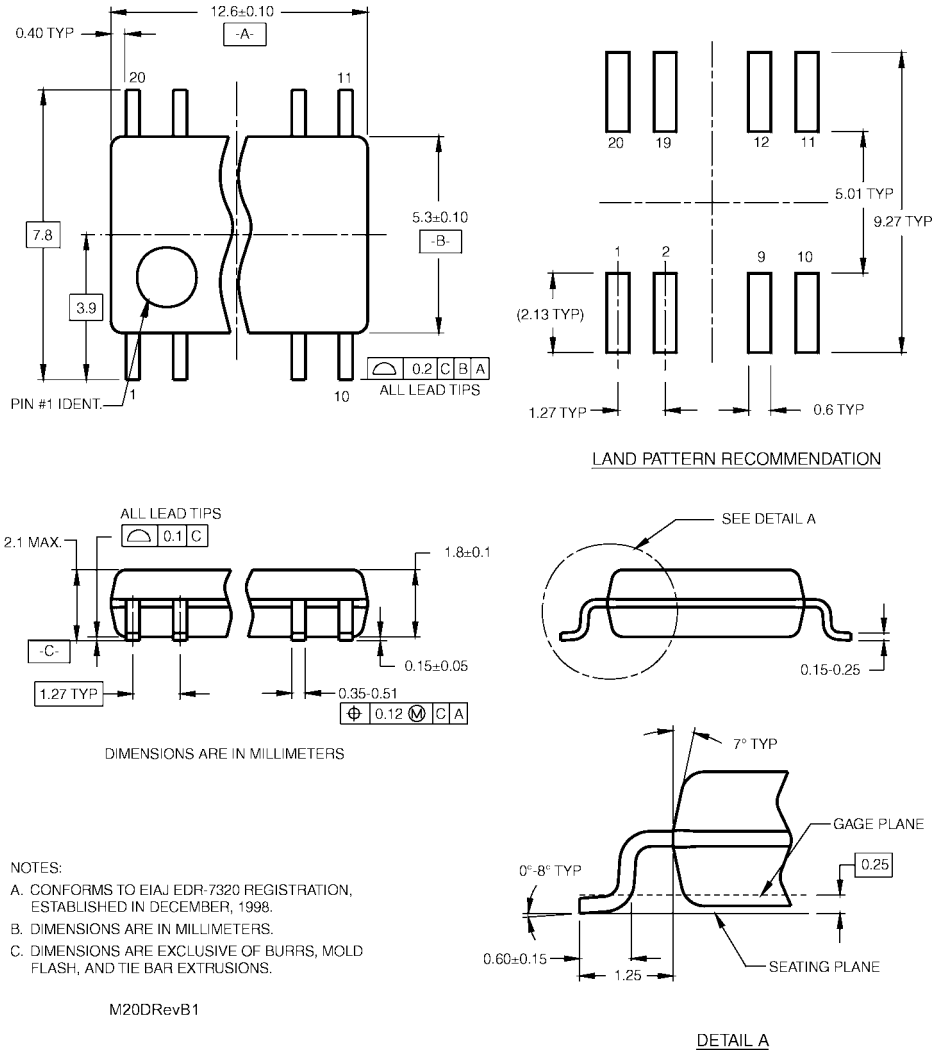
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

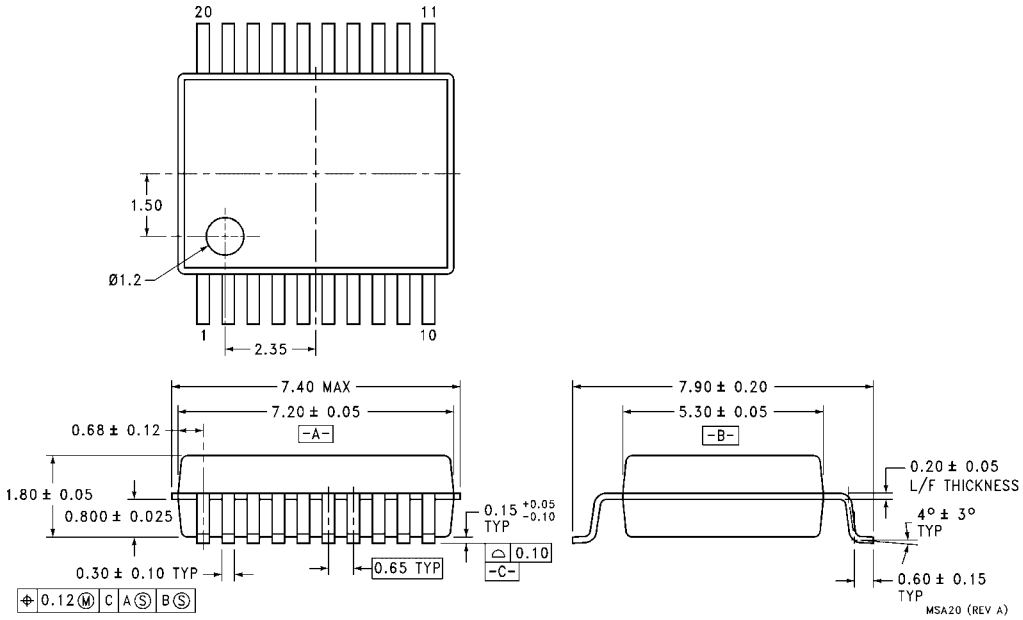
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

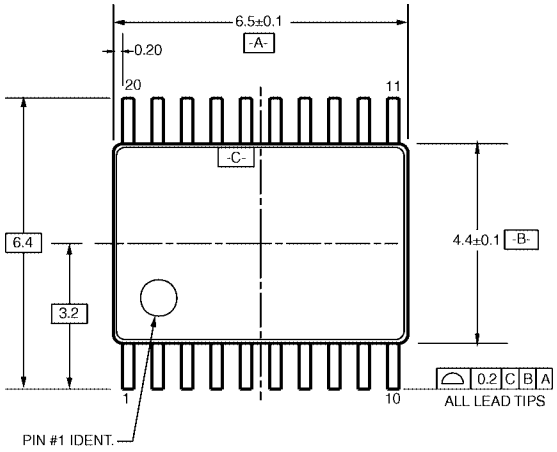
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

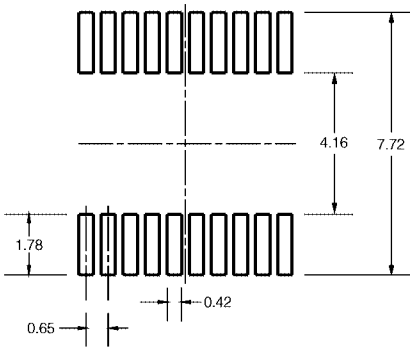
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



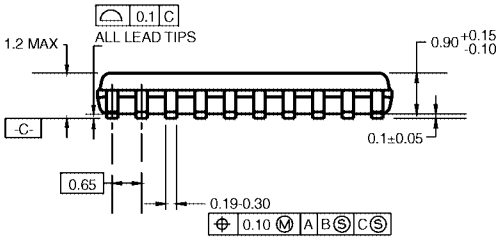
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

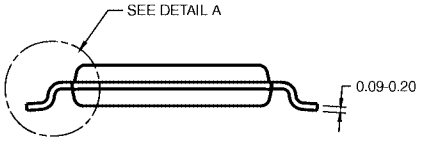
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

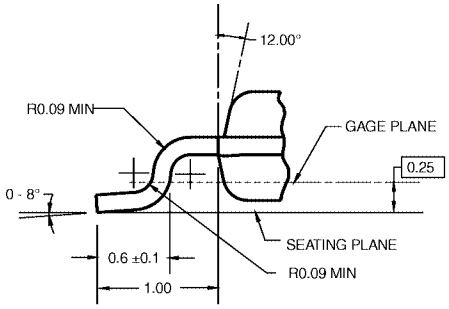
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

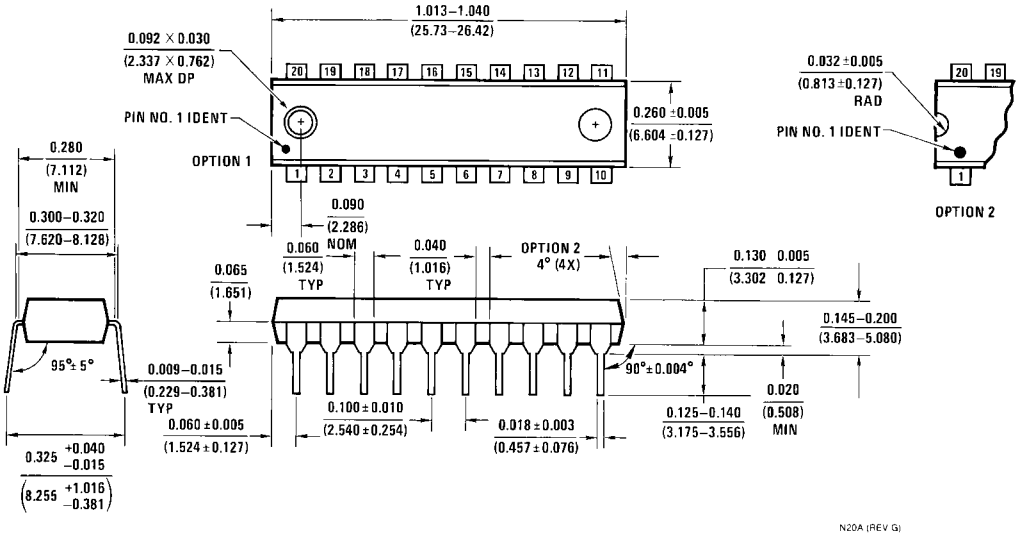
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

September 1991
Revised November 1999

74ABT245
Octal Bi-Directional Transceiver with 3-STATE Outputs

General Description

The ABT245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 64 mA on both the A and B ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active HIGH) enables data from A Ports to B Ports; Receive (active LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

Features

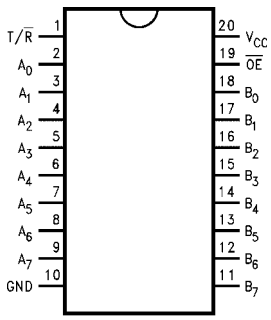
- Bidirectional non-inverting buffers
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch-free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Disable time is less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT245CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT245CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT245CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT245CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT245CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

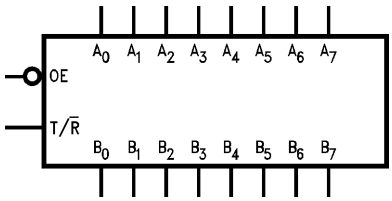
Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
$T/\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Logic Symbol

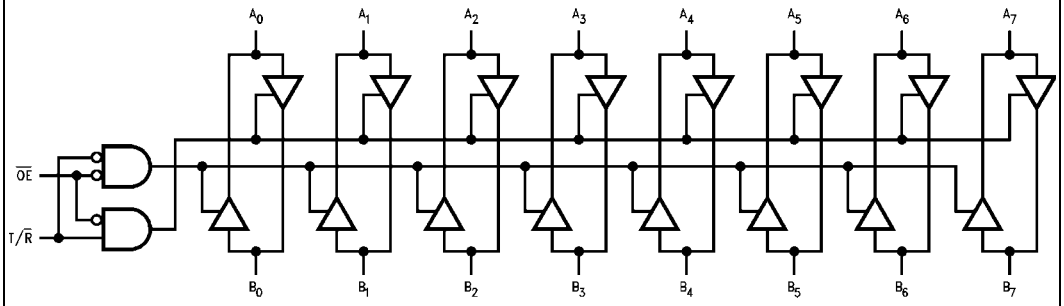


Truth Table

Inputs		Output
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA ($\overline{OE}$, T/$\overline{R}$)
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA (A_n, B_n)
			2.0			V	Min	I_{OH} = −32 mA (A_n, B_n)
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current				1	µA	Max	V_{IN} = 2.7V ($\overline{OE}$, T/$\overline{R}$)
					1			V_{IN} = V_{CC} ($\overline{OE}$, T/$\overline{R}$)
I_{BVI}	Input HIGH Current Breakdown Test				7	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, T/$\overline{R}$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)				100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current				−1	µA	Max	V_{IN} = 0.5V ($\overline{OE}$, T/$\overline{R}$)
					−1			V_{IN} = 0.0V ($\overline{OE}$, T/$\overline{R}$)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA ($\overline{OE}$, T/$\overline{R}$) All Other Pins Grounded
I_{IH} + I_{OZH}	Output Leakage Current				10	µA	0 – 5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OE}$ = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current				−10	µA	0 – 5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test				100	µA	0.0	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current				50	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	µA	Max	$\overline{OE}$ = V_{CC}, T/$\overline{R}$ = GND or V_{CC}; All Other GND or V_{CC}
I_{CCT}	Additional	Outputs Enabled			2.5	mA		V_I = V_{CC} − 2.1V
	I_{CC}/Input	Outputs 3-STATE			2.5	mA	Max	$\overline{OE}$, T/$\overline{R}$ V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	µA		Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or GND.
I_{CCD}	Dynamic I_{CC}	No Load			0.1	mA/ MHz	Max	Outputs Open $\overline{OE}$ = GND, T/$\overline{R}$ = GND or V_{CC} One Bit Toggling, 50% Duty Cycle

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	T_A = 25°C (Note 3)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.3	–1.0		V	5.0	T_A = 25°C (Note 3)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T_A = 25°C (Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.7		V	5.0	T_A = 25°C (Note 4)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		0.9	0.6	V	5.0	T_A = 25°C (Note 4)

Note 3: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 4: Max number of data inputs (n) switching. n-1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.1	3.6	1.0	4.8	1.0	3.6	ns
t_{PHL}	Data to Outputs	1.0	2.4	3.6	1.0	4.8	1.0	3.6	
t_{PZH}	Output Enable	1.5	3.2	6.0	1.0	6.7	1.5	6.0	ns
t_{PZL}	Time	1.5	3.7	6.0	2.0	7.5	1.5	6.0	
t_{PHZ}	Output Disable	1.0	3.6	6.1	1.7	7.4	1.0	6.1	ns
t_{PLZ}	Time	1.0	3.3	5.6	1.7	6.5	1.0	5.6	

Extended AC Electrical Characteristics

(SOIC package)

Symbol	Parameter	−40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 8 Outputs Switching (Note 6)			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 7)		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 8 Outputs Switching (Note 8)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.5	ns
t_{PHL}	Data to Outputs	1.5		5.0	1.5	6.0	2.5	8.5	
t_{PZH}	Output Enable Time	1.5		6.5	2.5	7.5	2.5	9.5	ns
t_{PZL}		1.5		6.5	2.5	7.5	2.5	11.0	
t_{PHZ}	Output Disable Time	1.0		6.5	(Note 9)		(Note 9)		ns
t_{PLZ}		1.0		5.6					

Note 6: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 7: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 8: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 9: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

(SOIC package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 10)	Pin to Pin Skew HL Transitions	1.3	2.3	ns
t_{OSLH} (Note 10)	Pin to Pin Skew LH Transitions	1.0	1.8	ns
t_{PS} (Note 14)	Duty Cycle LH–HL Skew	2.0	3.5	ns
t_{OST} (Note 10)	Pin to Pin Skew LH/HL Transitions	2.0	3.5	ns
t_{PV} (Note 11)	Device to Device Skew LH/HL Transitions	2.0	3.5	ns

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 11: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 13: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

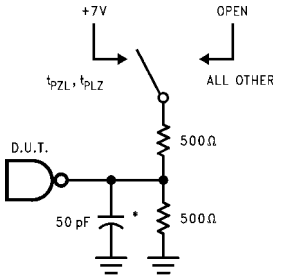
Note 14: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$ ($\overline{OE}$, $T/\overline{R}$)
$C_{I/O}$ (Note 15)	I/O Capacitance	11.0	pF	$V_{CC} = 5.0V$ (A_n, B_n)

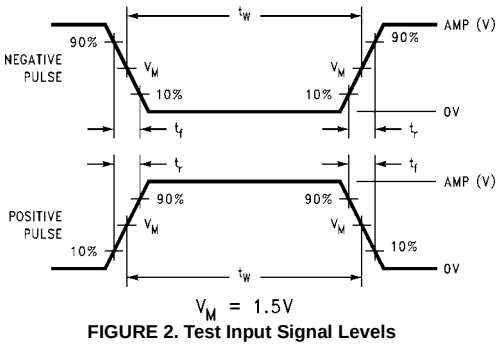
Note 15: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load



V_M = 1.5V

FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

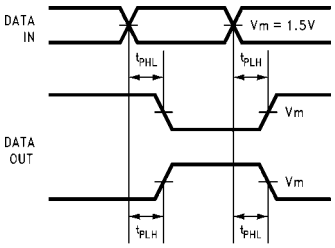


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

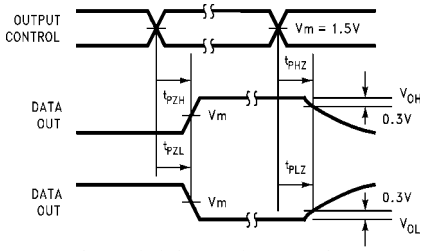


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

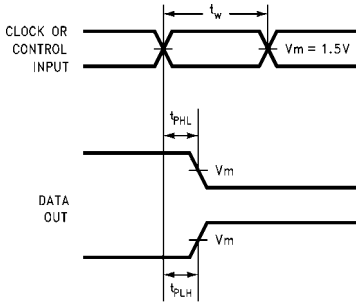


FIGURE 5. Propagation Delay, Pulse Width Waveforms

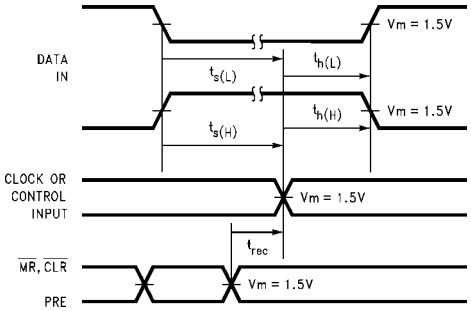
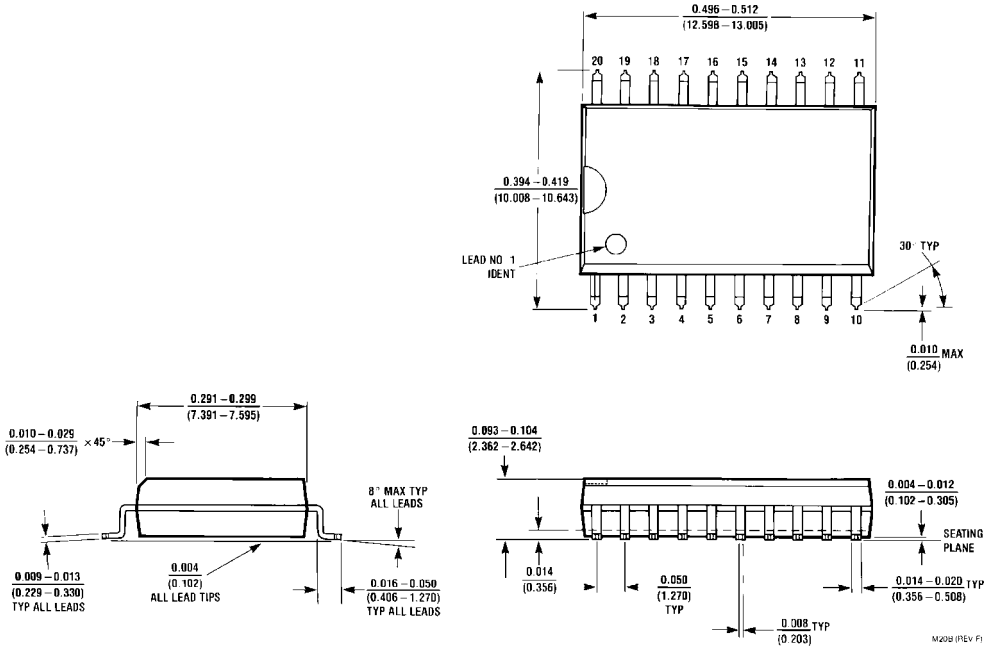


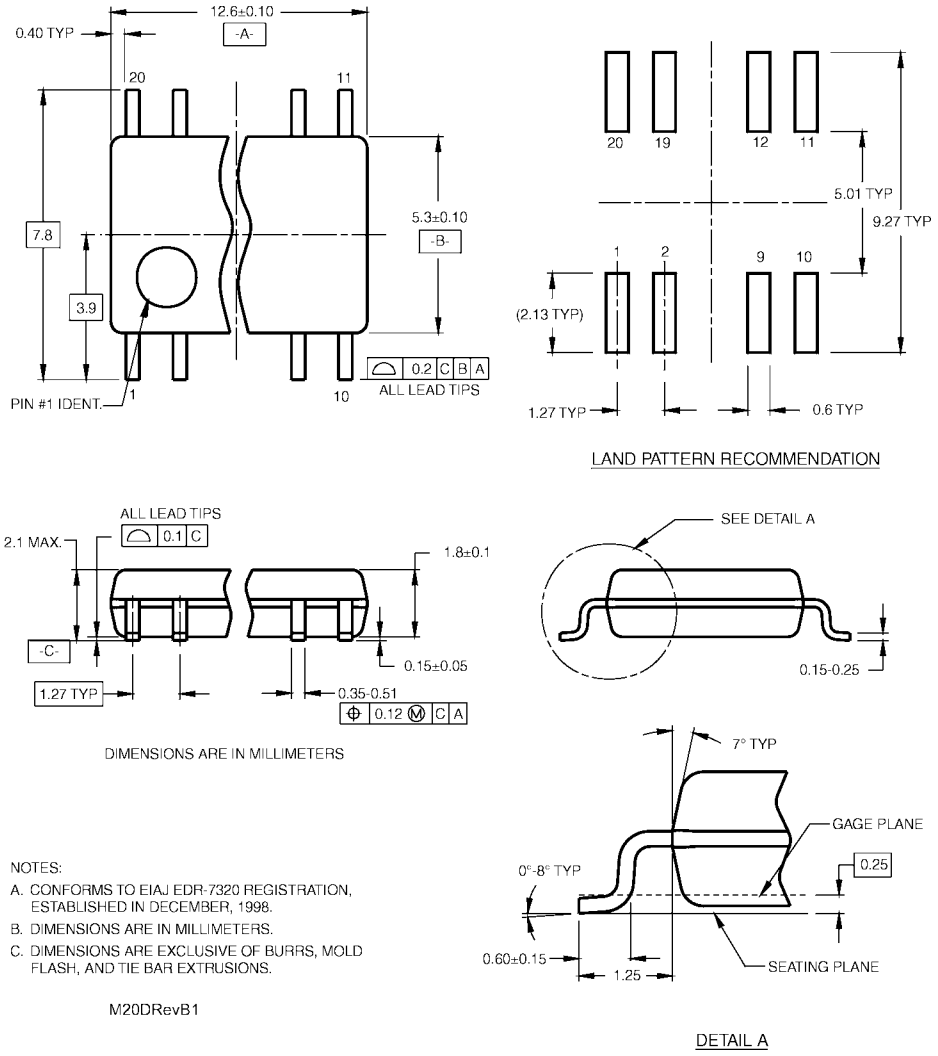
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

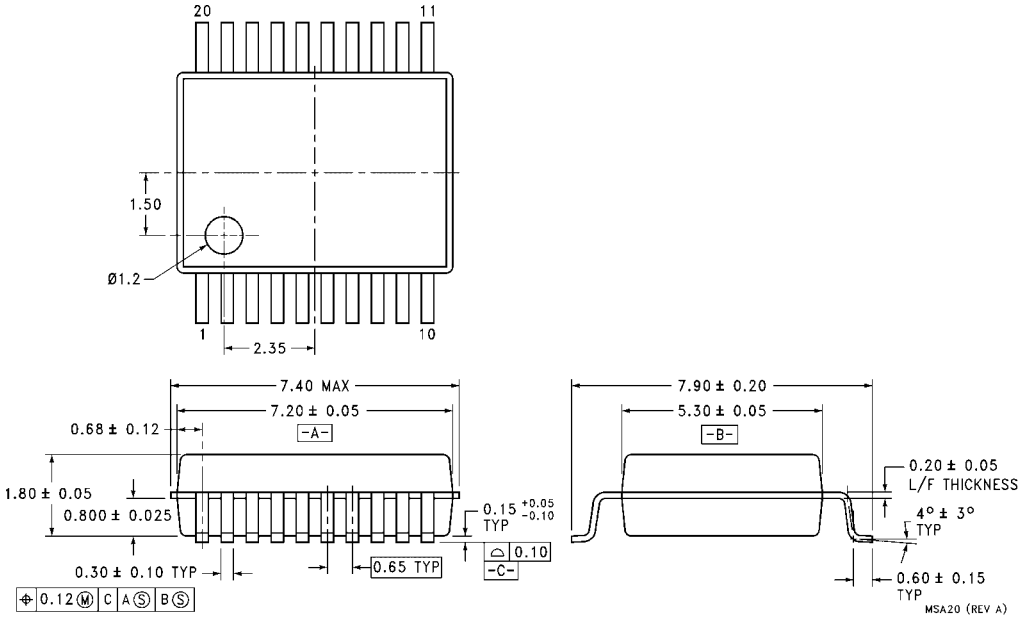
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

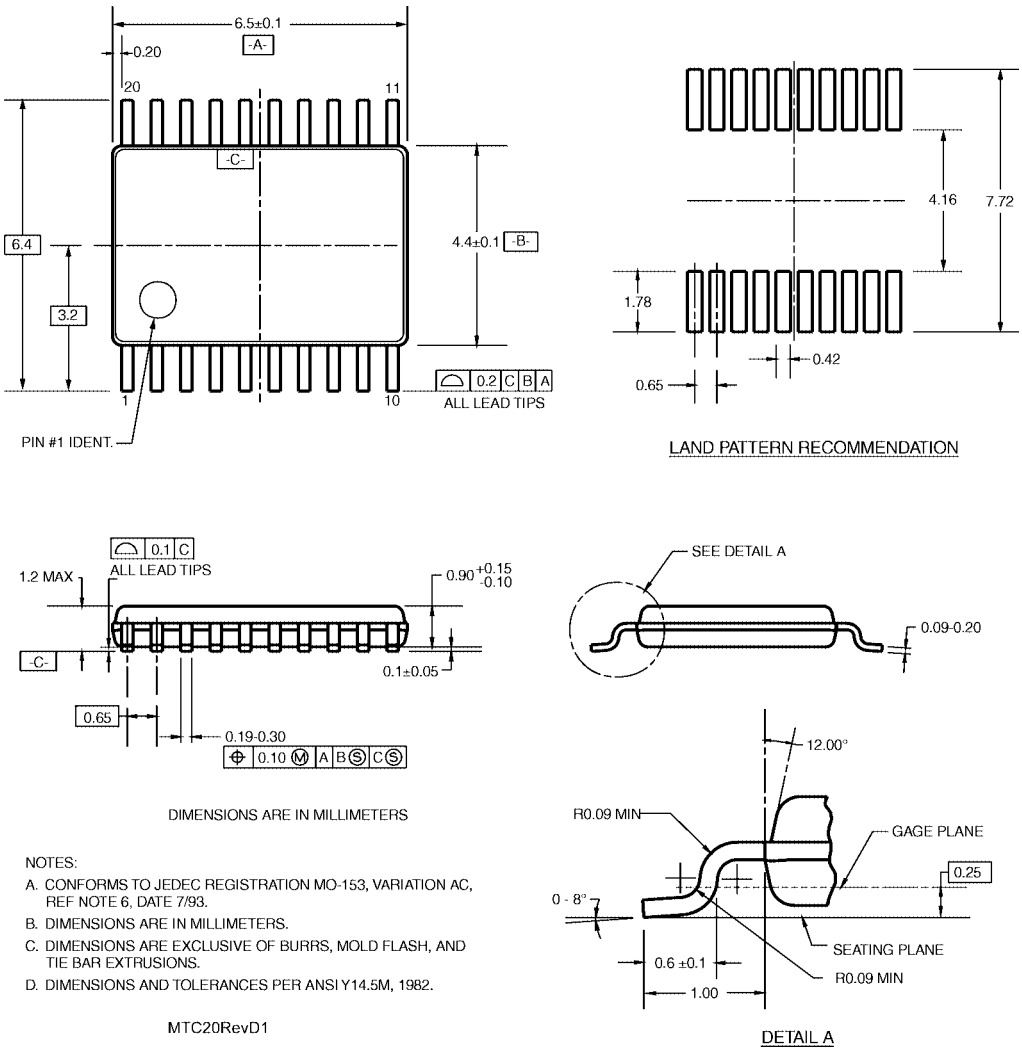
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

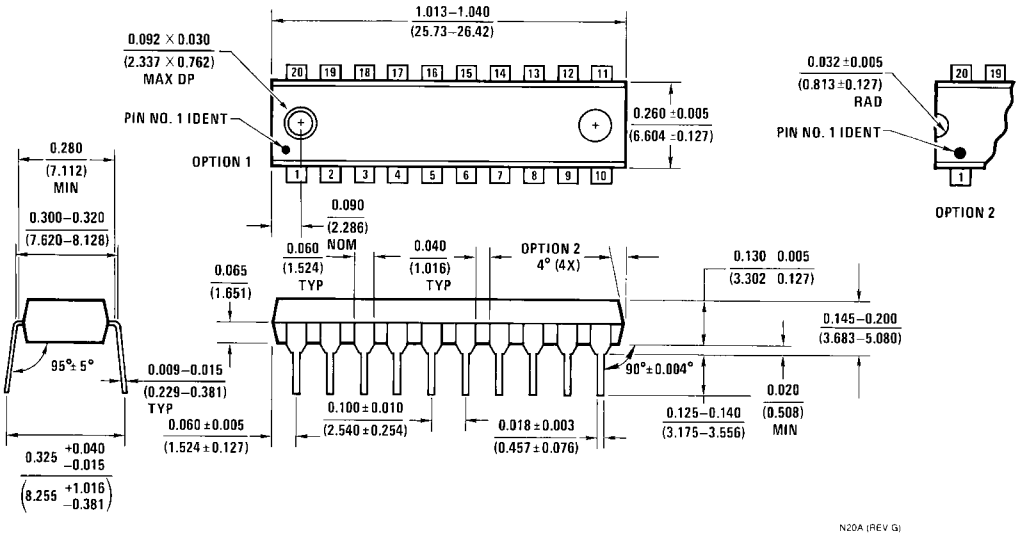
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

September 1992
Revised November 1999

74ABT2541
Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The ABT2541 is an octal buffer and line driver designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers, and bus-oriented transmitters/receivers. Functionally identical to the ABT541.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

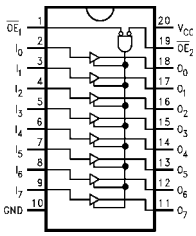
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneously switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

Ordering Code:

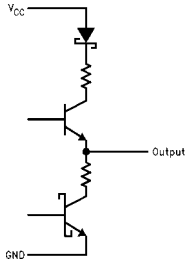
Order Number	Package Number	Package Description
74ABT2541CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT2541CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT2541CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT2541CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending "X" to the ordering code.

Connection Diagram



Schematic of Each Output



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.8	V	Min	I_{OL} = 15 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 4)	No Load			0.1	mA/MHz	Max	Outputs OPEN $\overline{OE}_n$ = GND (Note 3) One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8 bit toggling, I_{CCD} < 0.8 mA/MHz.

DC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.6	0.8	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−0.5	−0.4		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.4		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of data inputs (n) switching. n-1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Outputs	1.0	2.3	3.6	1.0	3.6	ns
t_{PHL}		1.0	3.3	4.1	1.0	4.1	
t_{PZH}	Output Enable Time	1.5	3.7	6.0	1.5	6.0	ns
t_{PZL}		1.5	4.3	6.5	1.5	6.5	
t_{PHZ}	Output Disable Time	1.0	3.5	6.0	1.0	6.0	ns
t_{PLZ}		1.0	3.7	5.6	1.0	5.6	

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	−40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 8 Outputs Switching (Note 8)			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 9)		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 8 Outputs Switching (Note 10)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Maximum Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.5	ns
t_{PHL}	Data to Outputs	1.5		5.5	1.5	10.0	2.5	11.0	
t_{PZH}	Output Enable Time	1.5		6.5	2.5	7.5	2.5	9.5	ns
t_{PZL}		1.5		7.0	2.5	11.0	2.5	12.5	
t_{PHZ}	Output Disable Time	1.0		6.0	(Note 11)		(Note 11)		ns
t_{PLZ}		1.0		6.0					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew HL Transitions	1.3	2.3	ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Transitions	1.0	1.8	ns
t_{PS} (Note 15)	Duty Cycle LH–HL Skew	2.0	5.0	ns
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Transitions	2.0	5.0	ns
t_{PV} (Note 16)	Device to Device Skew LH/HL Transitions	2.0	5.0	ns

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 13: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 15: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

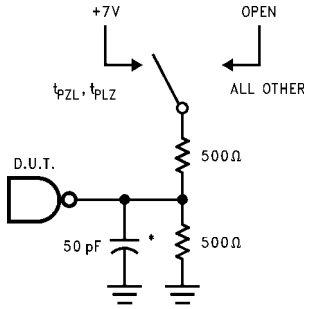
Note 16: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 17)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency f = 1 MHz; per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance.

FIGURE 1. Standard AC Test Load

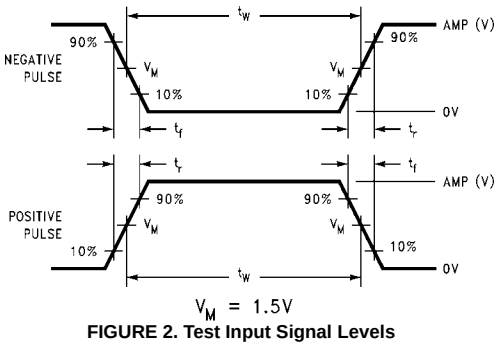


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

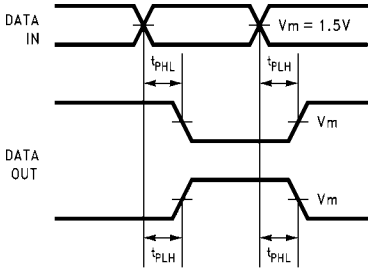


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

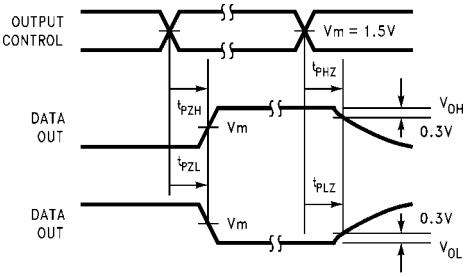


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

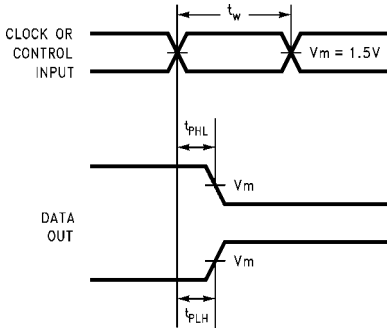


FIGURE 5. Propagation Delay, Pulse Width Waveforms

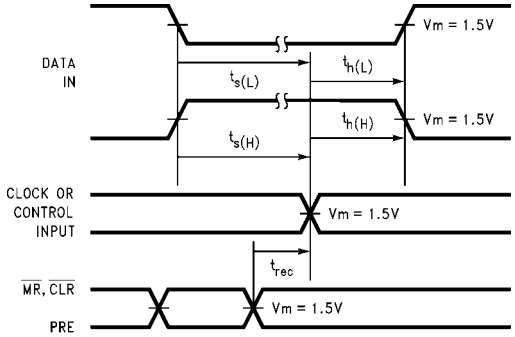
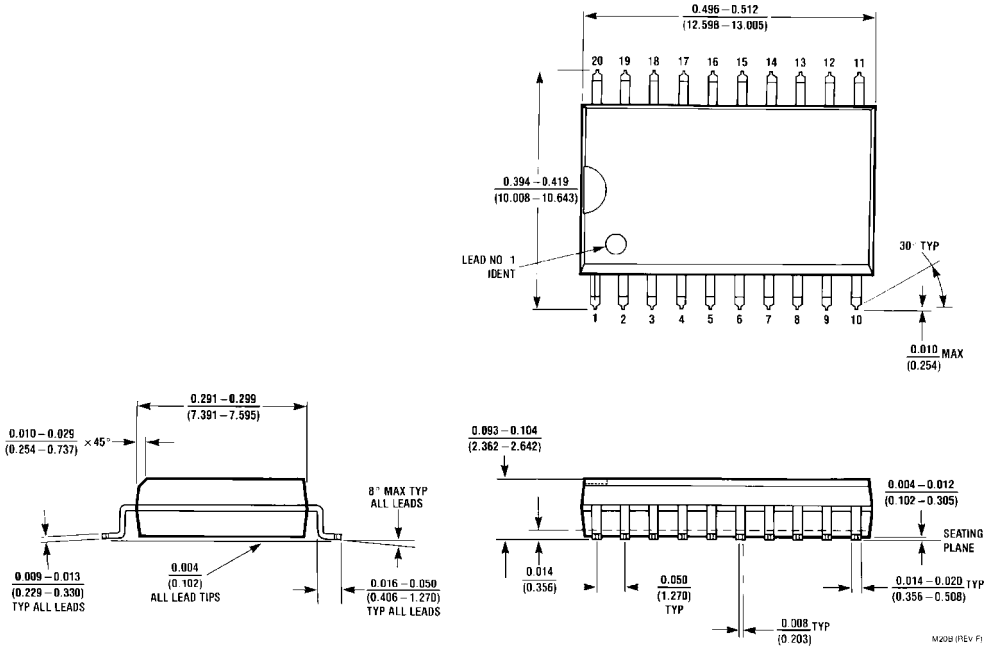


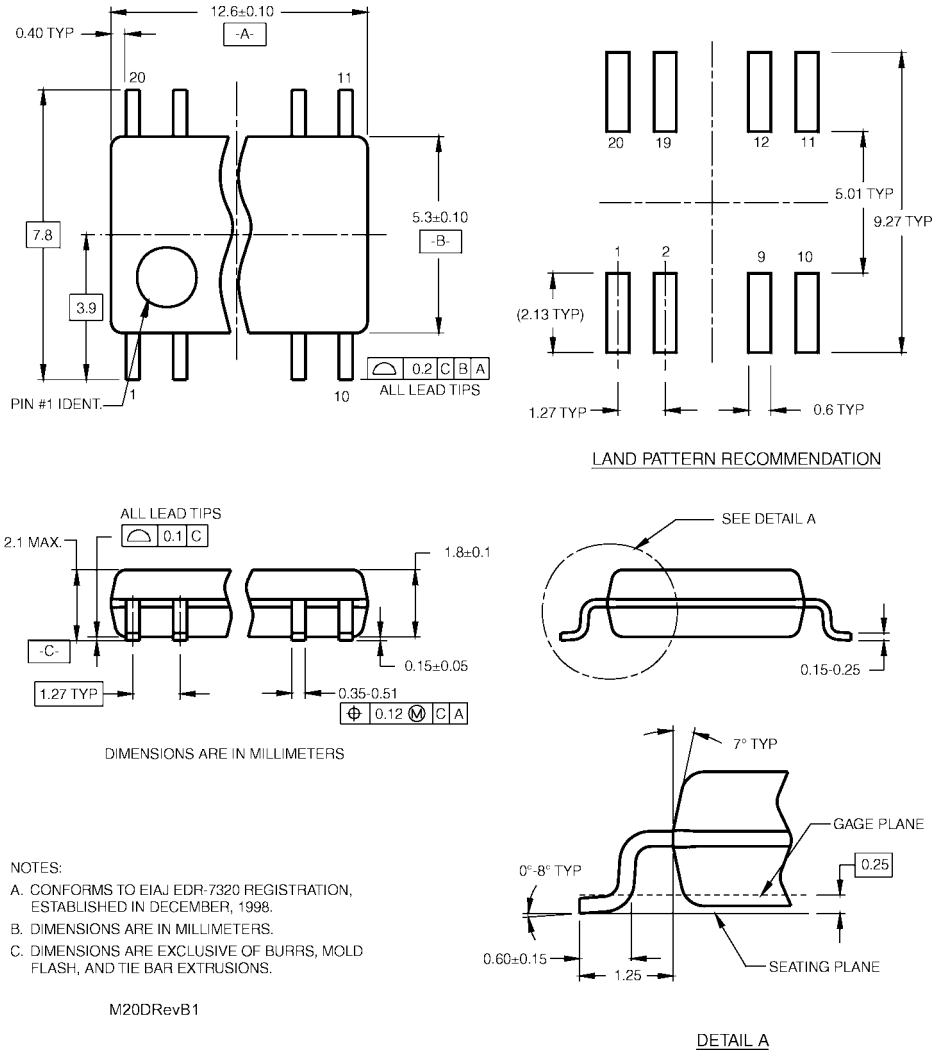
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

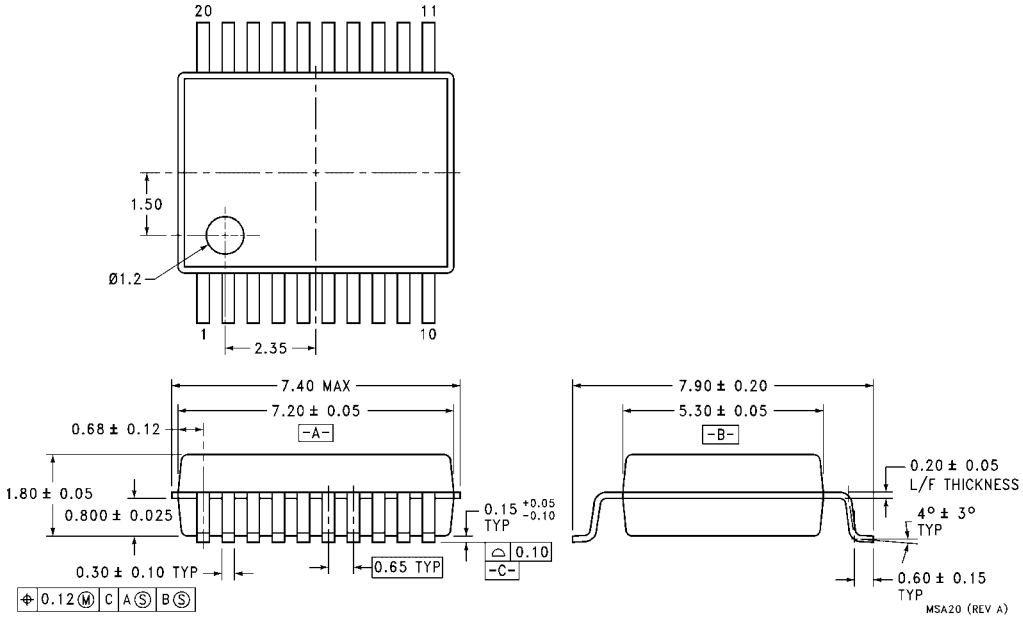
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

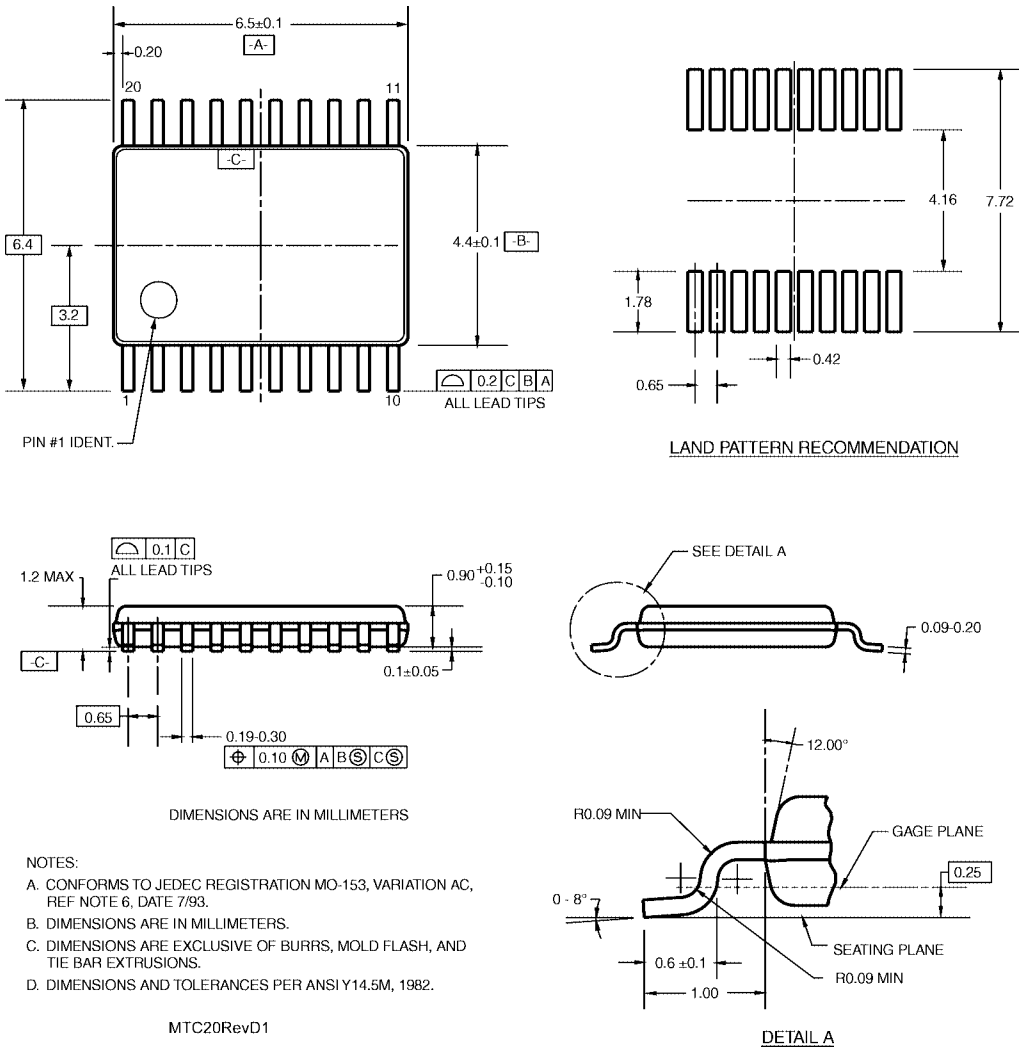
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1993
Revised November 1999

74ABT273
Octal D-Type Flip-Flop

General Description

The ABT273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

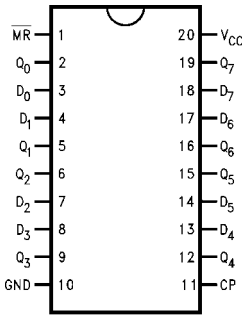
- Eight edge-triggered D-type flip-flops
- Buffered common clock
- Buffered, asynchronous Master Reset
- See ABT377 for clock enable version
- See ABT373 for transparent latch version
- See ABT374 for 3-STATE version
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Disable time less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT273CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT273CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT273CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT273CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

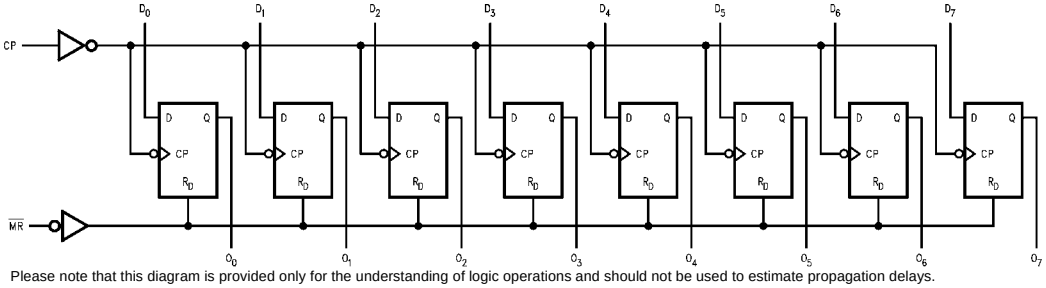
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset (Active LOW)
CP	Clock Pulse Input (Active Rising Edge)
Q_0–Q_7	Data Outputs

Truth Table

Operating Mode	Inputs			Output
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load “1”	H	⌐	h	H
Load “0”	H	⌐	l	L

H = HIGH Voltage Level steady state
h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH clock transition
L = LOW Voltage Level steady state
l = LOW Voltage Level one setup time prior to the LOW-to-HIGH clock transition
X = Immaterial
⌐ = LOW-to-HIGH clock transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to +4.75V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
(Across Comm Operating Range)	
Over Voltage Latchup	V_{CC} + 4.5V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.5 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −32 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			1 1	μA	Max	V_{IN} = 2.7V (Note 3) V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−1 −1	μA	Max	V_{IN} = 0.5V (Note 3) V_{IN} = 0.0V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	μA	Max	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current			50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I_{CCT}	Maximum I_{CC}/Input Outputs Enabled			1.5	mA	Max	V_I = V_{CC} − 2.1V Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load			0.3	mA/ MHz	Max	Outputs Open (Note 4) One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.5 mA/MHz.

AC Electrical Characteristics

(SSOIC package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150	200		150		150		MHz
t_{PLH}	Propagation Delay	2.0		6.0	1.0	7.0	2.0	6.0	ns
t_{PHL}	CP to O_n	2.8		6.8	1.0	7.5	2.8	6.8	
t_{PHL}	Propagation Delay $\overline{MR}$ to O_n	2.5		7.4	1.0	8.2	2.5	7.4	ns

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH	2.0		2.0		2.0		ns
$t_S(L)$	or LOW D_n to CP	2.5		2.5		2.5		
$t_H(H)$	Hold Time, HIGH	1.2		1.4		1.2		ns
$t_H(L)$	or LOW D_n to CP	1.2		1.4		1.2		
$t_W(H)$	Pulse Width, CP,	3.3		3.3		3.3		ns
$t_W(L)$	HIGH or LOW	3.3		3.3		3.3		
$t_W(L)$	Master Reset Pulse Width, LOW	3.3		3.3		3.3		ns
t_{REC}	Recovery Time $\overline{MR}$ to CP	2.0		2.0		2.0		ns

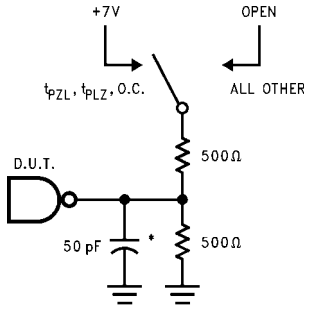
Capacitance

(SOIC package)

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9	pF	$V_{CC} = 5.0V$

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-833, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

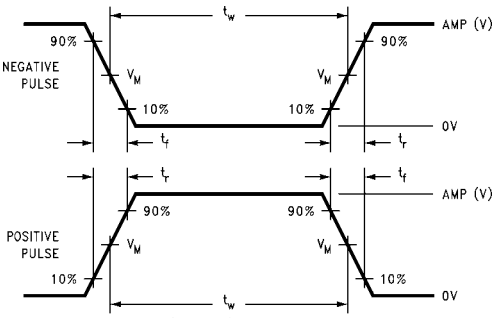


FIGURE 2. V_M = 1.5V Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

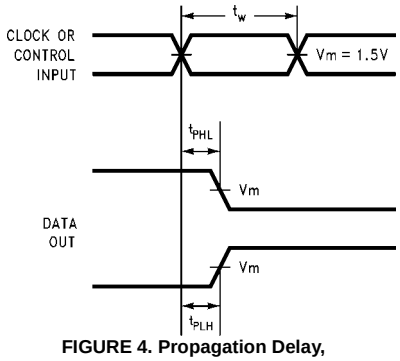


FIGURE 4. Propagation Delay, Pulse Width Waveforms

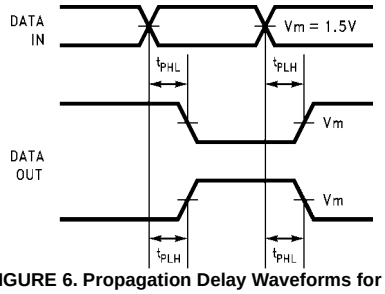


FIGURE 6. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

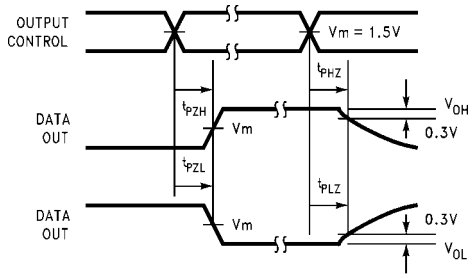


FIGURE 5. 3-STATE Output HIGH and LOW Enable and Disable Times

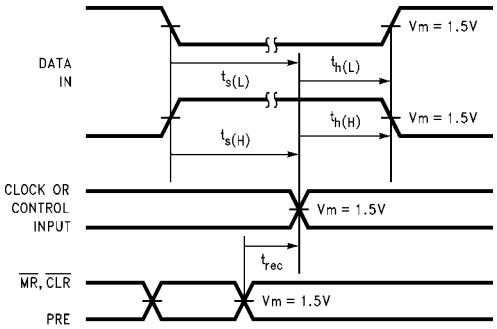
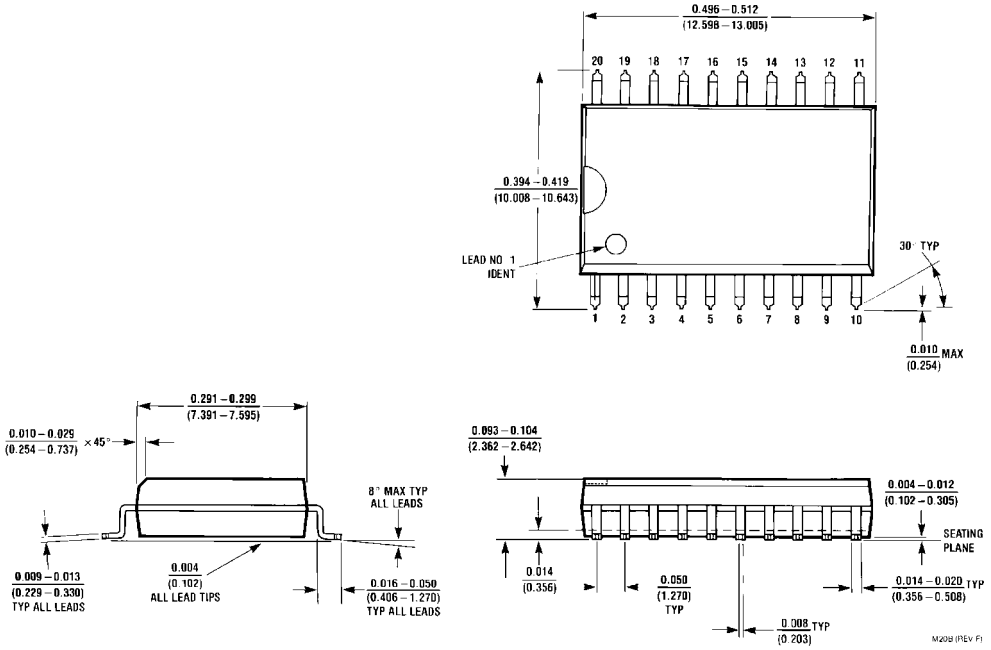


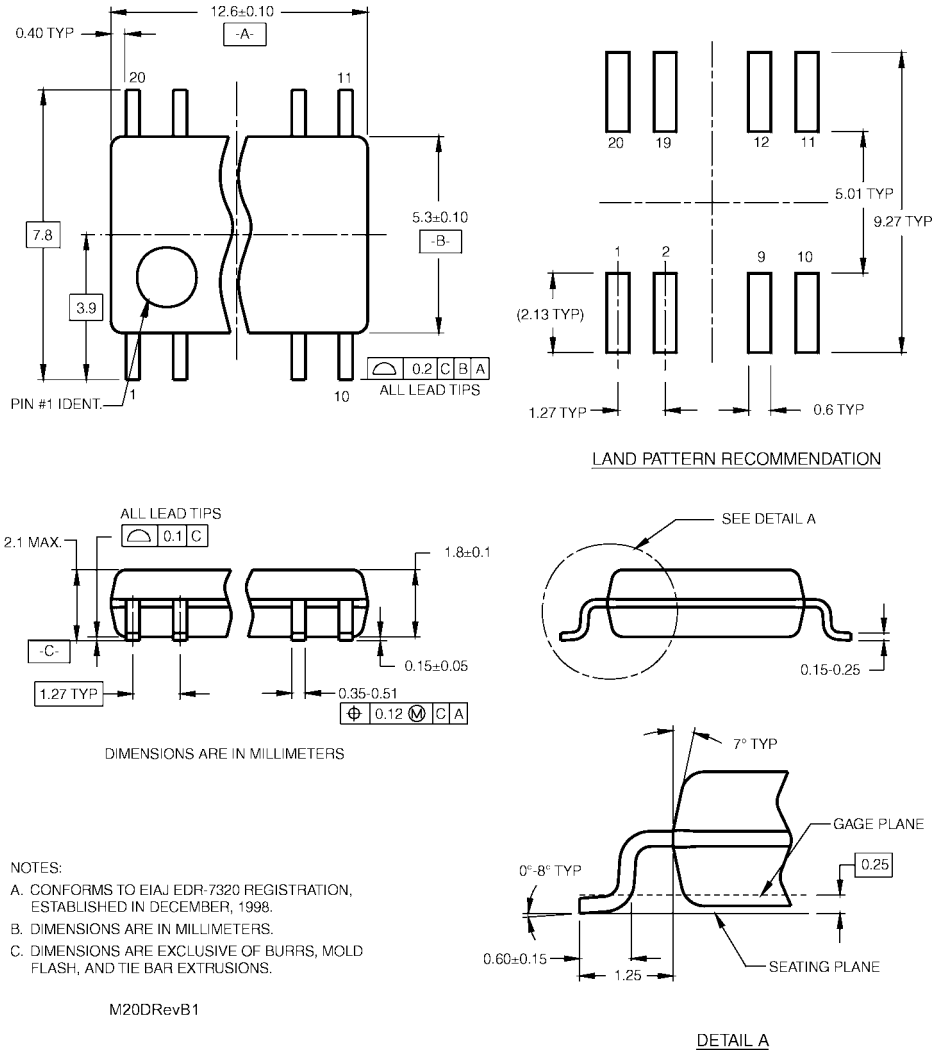
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

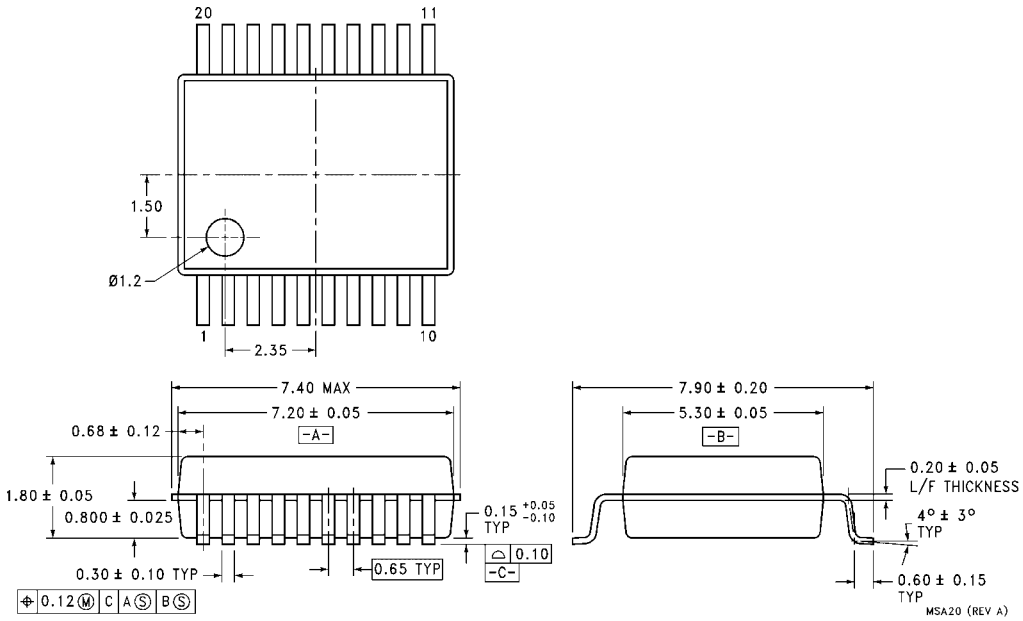
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

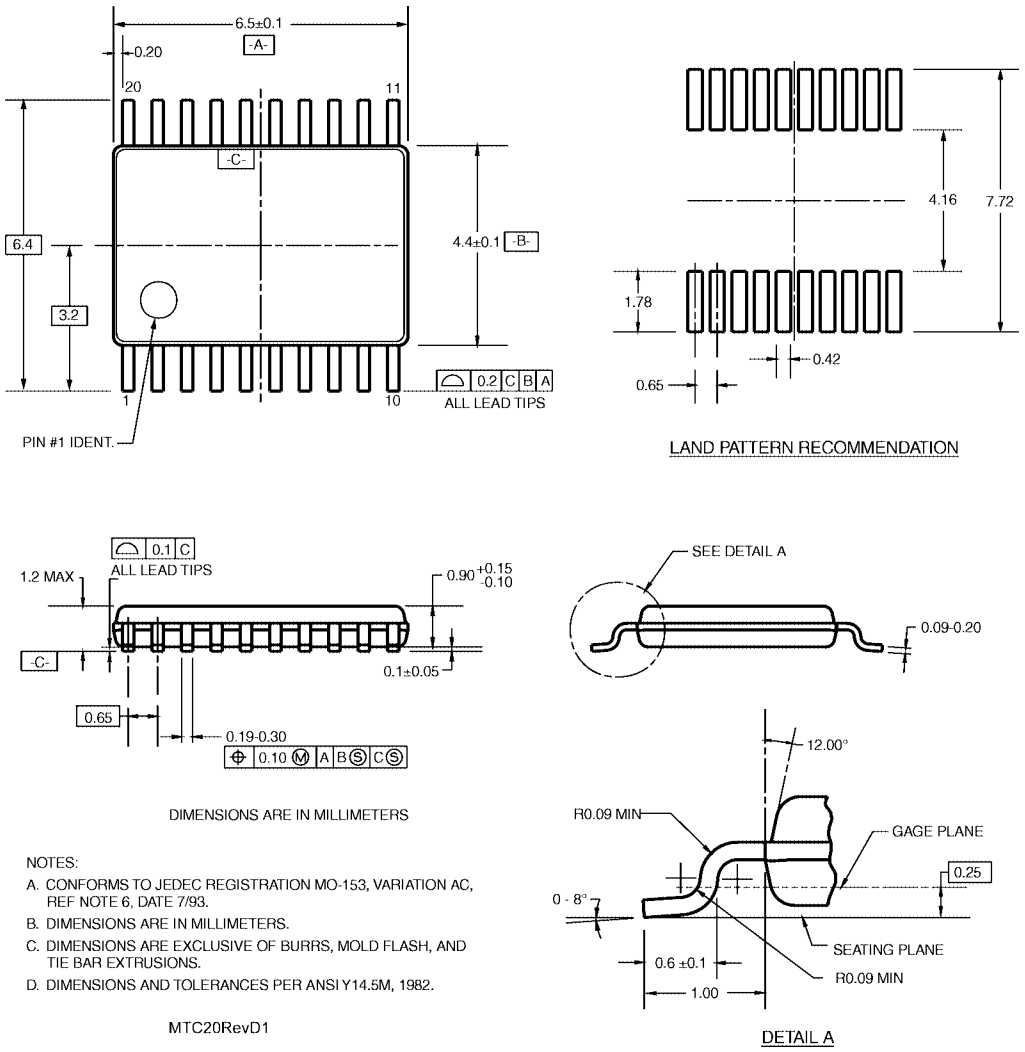
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1992
Revised November 1999

74ABT2952
Octal Registered Transceiver

General Description

The ABT2952 is an octal registered transceiver. Two 8-bit back to back registers store data flowing in both directions between two bidirectional buses. Separate clock, clock enable and 3-STATE output enable signals are provided for each register. The output pins are guaranteed to source 32 mA and to sink 64 mA.

Features

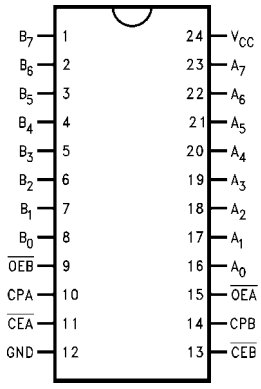
- Separate clock, clock enable and 3-STATE output enable provided for each register
- A and B output sink capability of 64 mA source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT2952CSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT2952CMSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT2952CMTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7	A-Register Inputs/B-Register 3-STATE Outputs
B_0–B_7	B-Register Inputs/A-Register 3-STATE Outputs
$\overline{OEA}$	Output Enable A-Register
CPA	A-Register Clock
$\overline{CEA}$	A-Register Clock Enable
$\overline{OEB}$	Output Enable B-Register
CPB	B-Register Clock
$\overline{CEB}$	B-Register Clock Enable

Truth Table

Output Control

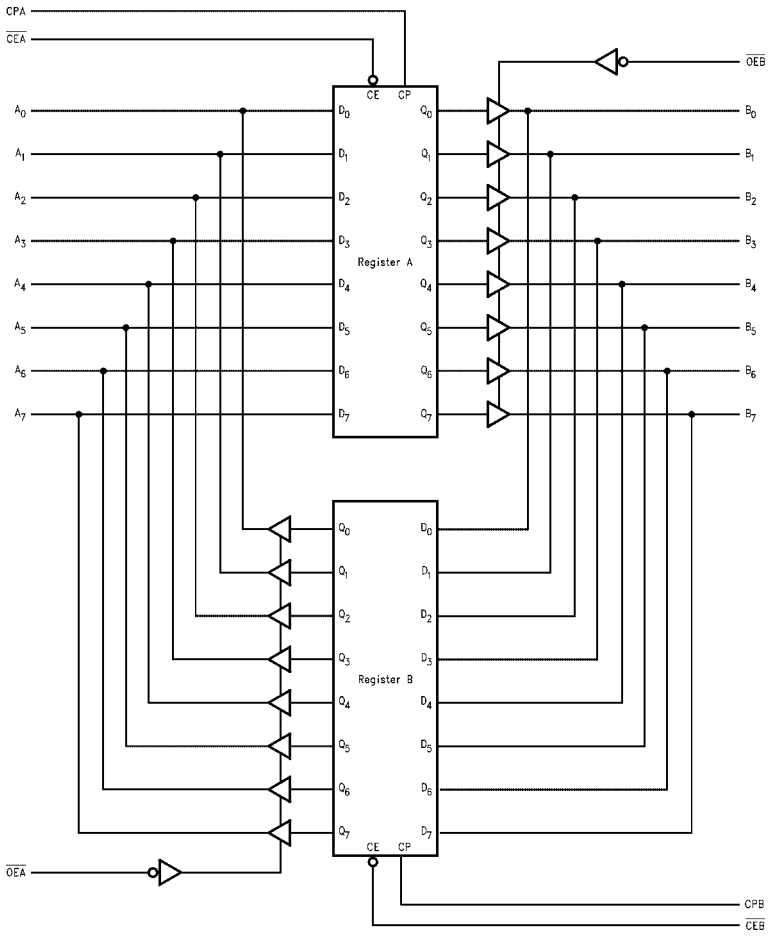
$\overline{OE}$	Internal Q	Output	Function
H	X	Z	Disable Outputs
L	L	L	Enable Outputs
L	H	H	

Register Function Table (Applies to A or B Register)

Inputs			Internal	Function
D	CP	$\overline{CE}$	Q	
X	X	H	NC	Hold Data
L	⌐	L	L	Load Data
H	⌐	L	H	

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable or	
Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5					I_{OH} = −3 mA (A_n, B_n)
		2.0					I_{OH} = −32 mA (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 μA (Non-I/O Pins) All Other Pins Grounded
I_{IH}	Input HIGH Current			1	μA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 3)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	μA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 3)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			10	μA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OEA}$ or $\overline{OEB}$ = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current			−10	μA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OEA}$ or $\overline{OEB}$ = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	μA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	μA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			250	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			50	μA	Max	Outputs 3-STATE; All Others GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V; All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 4)			0.18	mA/MHz	Max	Outputs Open $\overline{OEA}$ or $\overline{OEB}$ = GND, Non-I/O = GND or V_{CC} One Bit toggling, 50% duty cycle (Note 4)

Note 3: Guaranteed, but not tested.

Note 4: For 8-bit toggling, I_{CCD} < 1.4 mA/MHz.

DC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.6	0.8	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.2	–1.0		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.7		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at Low. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	200			200		MHz
t_{PLH}	Propagation Delay	1.5	3.4	5.3	1.5	5.3	ns
t_{PHL}	CPA or CPB to	1.5	3.6	5.3	1.5	5.3	
	A_n or B_n						
t_{PZH}	Output Enable Time	1.5	3.2	5.5	1.5	5.5	ns
t_{PZL}	$\overline{OEA}$ or $\overline{OEB}$ to	1.5	3.5	5.5	1.5	5.5	
	A_n or B_n						
t_{PHZ}	Output Disable Time	1.5	3.6	6.0	1.5	6.0	ns
t_{PLZ}	$\overline{OEA}$ or $\overline{OEB}$ to	1.5	3.2	6.0	1.5	6.0	
	A_n or B_n						

AC Operating Requirements

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = −40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	
t_S(H)	Setup Time, HIGH	2.5		2.5		ns
t_S(L)	or LOW A_n or B_n	2.5		2.5		
	to CPA or CPB					
t_H(H)	Hold Time, HIGH	1.5		1.5		ns
t_H(L)	or LOW A_n or B_n	1.5		1.5		
	to CPA or CPB					
t_S(H)	Setup Time, HIGH	2.5		2.5		ns
t_S(L)	or LOW $\overline{CEA}$ or $\overline{CEB}$	2.5		2.5		
	to CPA or CPB					
t_H(H)	Hold Time, HIGH	1.5		1.5		ns
t_H(L)	or LOW $\overline{CEA}$ or $\overline{CEB}$	1.5		1.5		
	to CPA or CPB					
t_W(H)	Pulse Width,	3.0		3.0		ns
t_W(L)	HIGH or LOW	3.0		3.0		
	CPA or CPB					

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 8)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF (Note 9)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 10)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	6.0	2.0	8.0	2.5	10.5	ns
t_{PHL}	CPA or CPB to A_n or B_n	1.5	6.0	2.0	8.0	2.5	10.5	
t_{PZH}	Output Enable Time	1.5	6.0	2.0	8.0	2.5	11.5	ns
t_{PZL}	$\overline{OEA}$ or $\overline{OEB}$ to A_n or B_n	1.5	6.0	2.0	8.0	2.5	11.5	
t_{PHZ}	Output Disable Time	1.5	6.0	(Note 11)		(Note 11)		ns
t_{PZL}	$\overline{OEA}$ or $\overline{OEB}$ to A_n or B_n	1.5	6.0					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew HL Transitions	1.0	1.5	ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Transitions	1.0	2.0	ns
t_{PS} (Note 15)	Duty Cycle LH–HL Skew	2.0	4.5	ns
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Transitions	2.1	4.5	ns
t_{PV} (Note 16)	Device to Device Skew LH/HL Transitions	2.5	5.0	ns

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 13: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

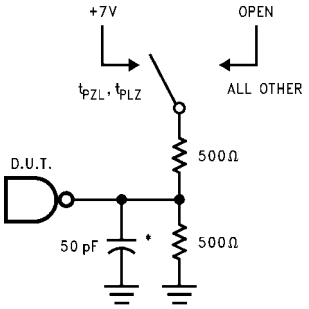
Note 16: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$ (Non I/O Pins)
$C_{I/O}$ (Note 17)	Output Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 17: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

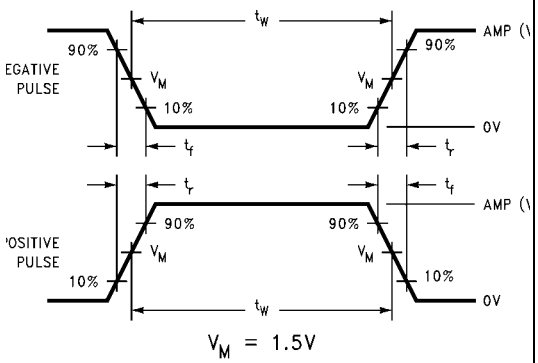


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Input Signal Requirements

AC Waveforms

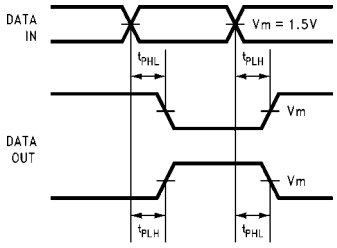


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

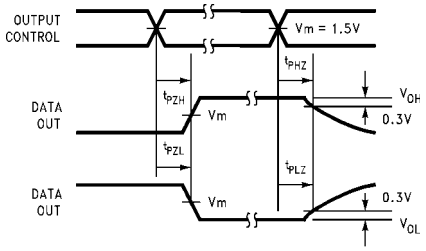


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

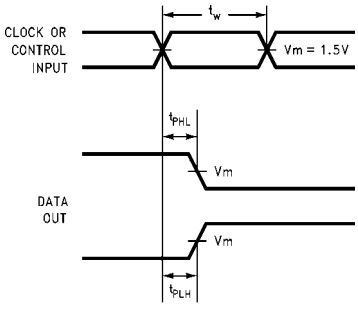


FIGURE 5. Propagation Delay, Pulse Width Waveforms

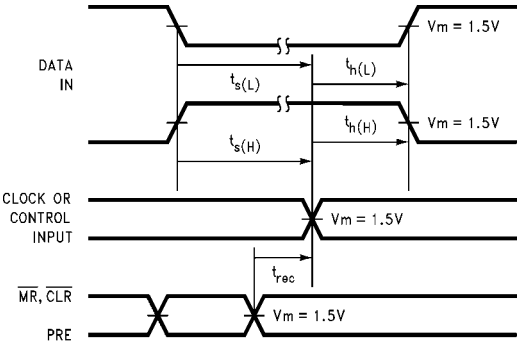
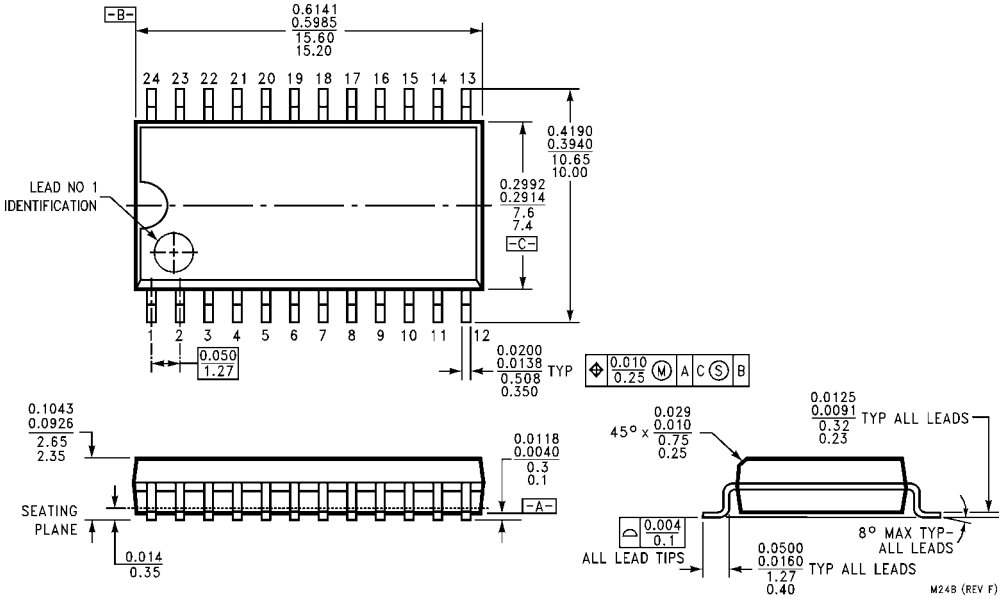
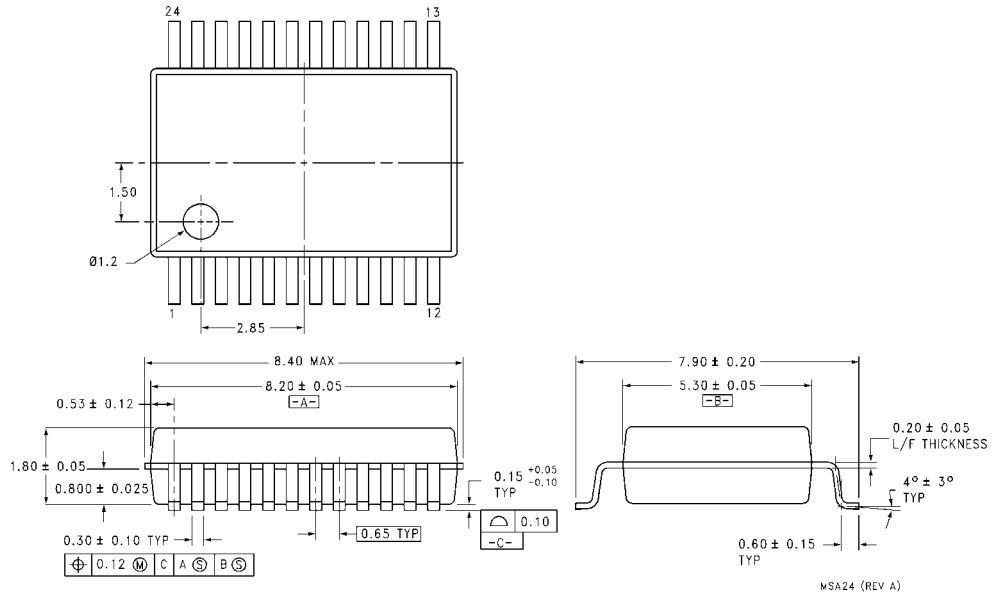


FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted

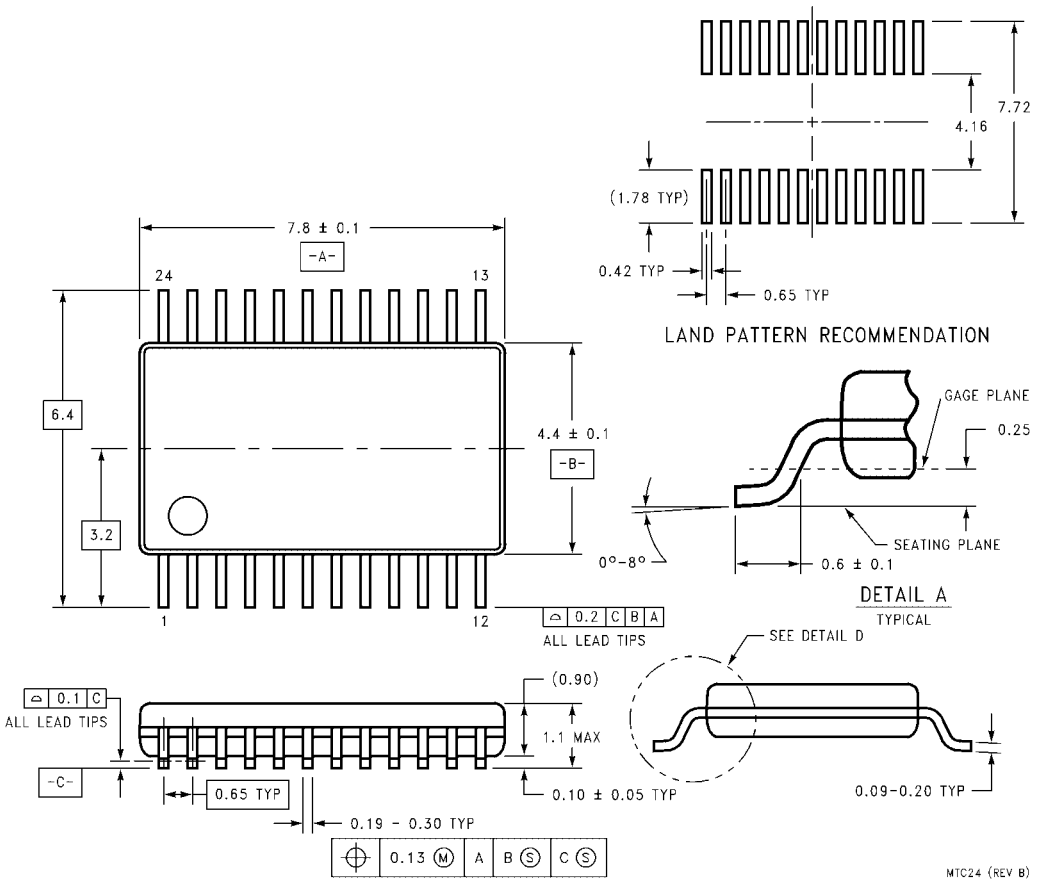


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

National Semiconductor

October 1995

74ABT3284
18-Bit Synchronous Datapath Multiplexer

General Description

The 74ABT3284 is a synchronous datapath buffer designed to transmit four 9-bit bytes of data onto one or two 9-bit bytes in 2:1 or 4:1 multiplexed configurations. In addition, the non-inverting transceiver supports bidirectional data transfer in transparent or registered modes. A data byte from any one of the six ports can be stored during transparent operation for later recall. Data input to any port may also be read back to itself for byte manipulation or system self-diagnostic purposes.

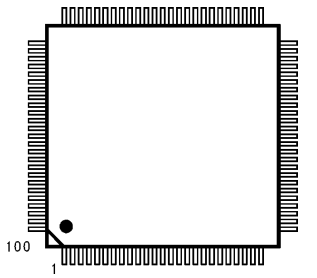
The 74ABT3284 is useful for interleaving data in memory applications or for use in bus-to-bus communications where variations in data word length or construction are required.

Features

- Advanced BiCMOS technology provides high speed at low power consumption
- 18-bit 2:1 or 9-bit 4:1 multiplexed modes
- Registered or transparent datapath operation
- Output enables and select lines have the option of being synchronized for pipelined operation
- Independent input, output register and control synchronizing clocks insure maximum timing flexibility
- Independent control signals insure functional flexibility
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Commercial	Package Number	Package Description
74ABT3284VJG	VJG100A	100-Lead (14mm x 14mm) Molded Plastic Quad Flatpak, JEDEC

Connection Diagram



TL/F/11582–1

Pin Assignment

Pin		Pin		Pin		Pin	
1	Mode_SO	26	V_{CC}	51	CP_IN	76	V_{CC}
2	CP_AX	27	A_8	52	$\overline{OEB}$	77	D_8
3	$\overline{OEC}$	28	A_7	53	LDBI	78	D_7
4	LDCI	29	A_6	54	LDBO	79	D_6
5	LDCO	30	GND	55	Mode_W	80	GND
6	SA_2X_1	31	A_5	56	YSEL	81	D_5
7	SA_2X_0	32	A_4	57	$\overline{OEY}$	82	D_4
8	X_0	33	A_3	58	Y_8	83	D_3
9	X_1	34	A_2	59	Y_7	84	D_2
10	GND	35	GND	60	GND	85	GND
11	X_2	36	A_1	61	Y_6	86	D_1
12	X_3	37	A_0	62	Y_5	87	D_0
13	X_4	38	V_{CC}	63	Y_4	88	V_{CC}
14	X_5	39	B_0	64	Y_3	89	C_0
15	X_6	40	B_1	65	Y_2	90	C_1
16	GND	41	GND	66	GND	91	GND
17	X_7	42	B_2	67	Y_1	92	C_2
18	X_8	43	B_3	68	Y_0	93	C_3
19	$\overline{OEX}$	44	B_4	69	LDDO	94	C_4
20	$XSEL_0$	45	B_5	70	LDDI	95	C_5
21	$XSEL_1$	46	GND	71	ASEL1	96	GND
22	LDAO	47	B_6	72	ASEL0	97	C_6
23	LDAI	48	B_7	73	$\overline{OED}$	98	C_7
24	$\overline{OEA}$	49	B_8	74	CP_XA	99	C_8
25	V_{CC}	50	V_{CC}	75	Mode_SC	100	V_{CC}

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Functional Description

The 74ABT3284 is a bi-directional registered data-path routing device which can multiplex/de-multiplex four 9-bit ''A-side'' data ports (Ports A, B, C, D) onto/from one 9-bit ''X-side'' port (Port X). Alternatively, it can be configured for mux/demux of two 18-bit data paths (Ports A and C, B and D) onto/from one 18-bit data path (Ports X and Y).

Each of the six 9-bit I/O ports have independent active low TRI-STATE® output enable control logic which can be configured to operate asynchronously or synchronously. With MODE__SO low, direct asynchronous output control is provided. With MODE__SO high, output enable control is asserted synchronously on the positive edge of the CP__IN clock. All I/O port inputs are continuously active allowing output state feedback.

The four A-side ports (A, B, C, D) contain independently enabled input and output data registers for storage of data passing in either direction. The input register (AIR, BIR, CIR, DIR) is loaded/held on the positive edge of CP__AX when the respective Load Control pin (LDAI, LDBI, LDCI, LDDI) is asserted high/low. The Input Registers can be loaded with data from the corresponding A-side port. The output register (AOR, BOR, COR, DOR) is loaded/held on the positive edge of CP__XA when the respective Load Control pin (LDAO, LDBO, LDCO, LDDO) is asserted high/low. The Output Registers can be loaded with data from Port X when MODE__WS is asserted low. When MODE__WS is asserted high, the Output Registers A and C can be loaded with Port X data and the B and D Output Registers can be loaded with data from Port Y.

When routing data from A-side to X-side, Data Path Control is provided for the following options via the SA2X inputs; Transparent mode where Input Register is bypassed but can simultaneously monitor A-side data; Registered Mode where X-side receives data from the selected Input Registers; Readback Mode where X-side receives data from the selected Output Registers. A-side data from Ports A, B, C, or D can be selected to Port X via the XSEL data path select inputs. Ports B or D can be selected to Port Y via the YSEL data path select input.

When routing data from X-side to A-side, Data Path Control is provided for the following options via the ASEL inputs; Transparent mode where Output Register is bypassed but can simultaneously monitor X-side data; Registered Mode where the A-side Port receives data from the corresponding Output Register; Readback Mode where the A-side Port receives data from the corresponding Input Registers. MODE__WS asserted low selects Port X data to be passed to Ports A, B, C, and D. With MODE__WS asserted high, Port X data is passed to Ports A and C with Port Y data passed to Ports B and D.

All Data Path Control Inputs and Input/Output Register Load Enable Inputs are active high and can be asserted asynchronously or synchronously. When MODE__SC is low, these inputs operate asynchronously. When MODE__SC is high, the inputs are asserted synchronously on the positive edge of the CP__IN clock.

When operating the Data Path Control and/or the Output Enable Input groups with MODE__SC and/or MODE__SO ''hard wired'' high for synchronous mode, a single pre-clock of CP__IN will be required following power-up to insure that all internal synchronous control registers are in the appropriate known state. if the application requires ''on the fly''' changes from asynchronous to synchronous operation, then the respective control/enable pin data must be pre-clocked via CP__IN and held steady prior to and during any low to high transition of the MODE__SO or MODE__SC to properly initiate the sync control registers for synchronous control mode.

Pin Descriptions

Pin Name	Description	Operation
$\overline{OEa}$	Output Enable Inputs (Active Low)	Sync/Async
LDaI	Load Enable Inputs for the Input Registers	Sync/Async
LDaO	Load Enable Inputs for the Output Registers	Sync/Async
ASEL(0,1)	A-Side Data Path Select Inputs	Sync/Async
SA2X(0,1)	X-Side Data Path Select Inputs	Sync/Async
XSEL(0,1)	X-Port Data Path Select Inputs	Sync/Async
YSEL	Y-Port Data Path Select Input	Sync/Async
MODE__W	Word Mode Select Input for the X/Y to A-Side Direction	Sync/Async
MODE__SO	Enable Input for Synchronous Output Enable Control	Async
MODE__SC	Enable Input for Synchronous Data Path Control	Async
CP__IN	Clock Input for Synchronous Control (Positive Edge Trigger)	
CP__AX	Clock Input for Input Registers (Positive Edge Trigger)	
CP__XA	Clock Input for Output Registers (Positive Edge Trigger)	

Function Tables

Output Enable Control Table

Inputs			Outputs	Control Mode	Function
$\overline{OE}$ (A, B, C, D, X, Y)	MODE__SO	CP__IN	Port A, B, C, D, X, Y		
L	L	X	ENABLE	ASYNC	ENABLED OUTPUT, I/O input always active
H	L	X	DISABLE	ASYNC	DISABLED OUTPUT, I/O input always active
(Notes 2, 3)	H (Note 1)	⎍	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SO must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs $\overline{OE}$ (A, B, C, D, X, Y) steady to preset internal registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: $\overline{OE}$ (A, B, C, D, X, Y) levels are synchronously asserted by the positive transition of CP__IN when MODE__SO is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

A Side Data Path Select Function Table

Inputs				Data Path		Control Mode	Function
ASEL(1)	ASEL(0)	MODE__SC	CP__IN	From Reg/Port	To Port		
L	L	L	X	(A, B, C, D) IR	A, B, C, D	ASYNC	Readback; Contents of Input Register (A, B, C, D) IR to Port (A, B, C, D)
L	H	L	X	(A, B, C, D) OR	A, B, C, D	ASYNC	Clocked Path; Contents of Output Register (A, B, C, D) OR to Port (A, B, C, D)
H	L	L	X	Port X	A, B, C, & D	ASYNC	Transparent Path; Port X to Port A, B, C, & D
H	H	L	X	Port X Port Y	A & C B & D	ASYNC	Transparent Path; Port X to Port A & C Transparent Path; Port Y to Port B & D
(Notes 2, 3)	(Notes 2, 3)	H (Note 1)	⎍	(Note 3)	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SC must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs ASEL(0) and ASEL(1) steady to preset internal registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: ASEL(0) and ASEL(1) levels are synchronously asserted by the positive transition of CP__IN when MODE__SC is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

Input Register Control Table

Inputs					Register	Control Mode	Function
Port (A, B, C, D)	LD(A, B, C, D) I	MODE__SC	CP__IN	CP__XA	(A, B, C, D) IR		
X	L	L	X	⎍	HOLD	ASYNC	HOLD; Input Register holds previous state.
L (H)	H	L	X	⎍	L (H)	ASYNC	LOAD; Port A, B, C, D clocked to Input Register (A, B, C, D) IR via CP__AX positive edge
(Note 3)	(Notes 2, 3)	H (Note 1)	⎍	(Note 3)	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SO must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs LDAI, LDBI, LDCI, and LDDI steady to preset internal registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: LDAI, LDBI, LDCI and LDDI levels are synchronously asserted by the positive transition of CP__IN when MODE__SC is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

Function Tables (Continued)

Output Register Control Table

Inputs							Output Register		Control Mode	Function
Port X	Port Y	LD(A, B, C, D) O	MODE__W	MODE__SC	CP__IN	CP__XA	(A, C) OR	(B, D) OR		
X	X	L	X	L	X	⌐	HOLD	HOLD	ASYNC	HOLD OR
L (H)	X	H	L	L	X	⌐	L (H)	L (H)	ASYNC	LOAD OR Port X to OR (A, B, C, D)
L (H)	L (H)	H	H	L	X	⌐	L (H)	L (H)	ASYNC	LOAD OR Port X to OR (A, C) Port Y to OR (B, D)
(Note 3)	(Note 3)	(Notes 2, 3)	(Notes 2, 3)	H (Note 1)	⌐	(Note 3)	(Note 3)	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SC must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs LDAO, LDBO, LDCO, LDDO and MODE__W steady to preset internal registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: LDAO, LDBO, LDCO, LDDO and MODE__W levels are synchronously asserted by the positive transition of CP__IN when MODE__SC is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

Function Tables (Continued)

1st Level X Side Data Path Select Function Table

Inputs				Data Path		Control Mode	Function
SA2X(1)	SA2X(0)	MODE__SC	CP__IN	From Reg/Port	To Internal Node		
L	L	L	X	A, B, C, D	(A, B, C, D) X	ASYNC	Transparent datapath from Port (A, B, C, D) to internal node (A, B, C, D) X
L	H	L	X	(A, B, C, D) IR	(A, B, C, D) X	ASYNC	Clocked Path; Contents of Input Register (A, B, C, D) IR to internal node (A, B, C, D) X
H	L	L	X	(A, B, C, D) OR	(A, B, C, D) X	ASYNC	Readback; contents of Output register (A, B, C, D) OR to internal node (A, B, C, D) X
H	H	L	X	GND	(A, B, C, D) X	ASYNC	Diagnostic; Select all 36 bits as low and pass to the internal node (A, B, C, D) X
(Notes 2, 3)	(Notes 2, 3)	H (Note 1)	⎍	(Note 3)	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SC must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs SA2X(0) and SA2X(1) steady to preset internal sync registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: SA2X(0) and SA2X(1) levels are synchronously asserted by the positive transition of CP__IN when MODE__SC is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

2nd Level X Side Data Path Select Function Table for Port X

Inputs				Data Path		Control Mode	Function
XSEL(1)	XSEL(0)	MODE__SC	CP__IN	From Internal Node	To Port		
L	L	L	X	AX	X	ASYNC	Internal Node AX to Port X
L	H	L	X	BX	X	ASYNC	Internal Node BX to Port X
H	L	L	X	CX	X	ASYNC	Internal Node CX to Port X
H	H	L	X	DX	X	ASYNC	Internal Node DX to Port X
(Notes 2, 3)	(Notes 2, 3)	H (Note 1)	⎍	(Note 3)	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SC must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs XSEL(0) and XSEL(1) steady to preset internal sync registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: XSEL(0) and XSEL(1) levels are synchronously asserted by the positive transition of CP__IN when MODE__SC is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

2nd Level X Side Data Path Select Function Table for Port Y

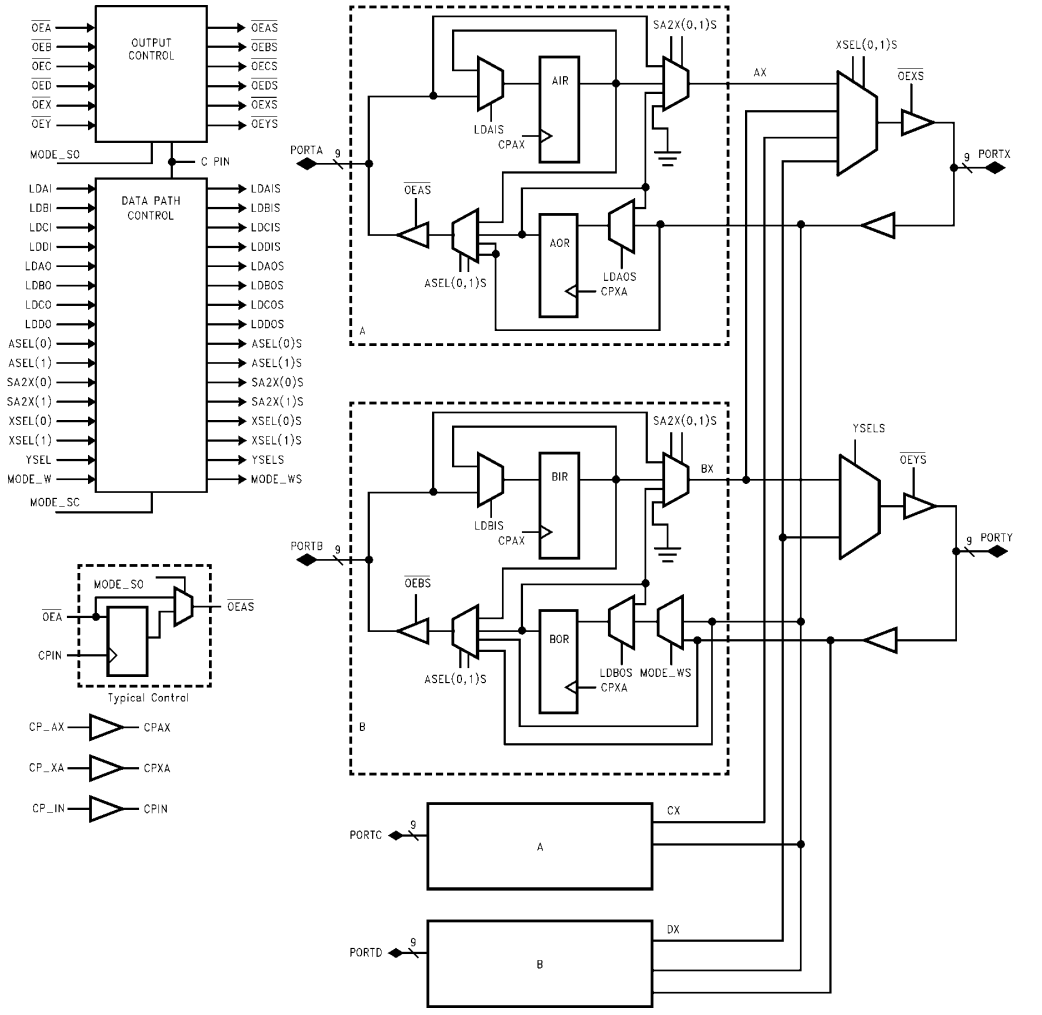
Inputs			Data Path		Control Mode	Function
YSEL	MODE__SC	CP__IN	From Internal Node	To Port		
L	L	X	BX	Y	ASYNC	Internal Node BX to Port Y
H	L	X	DX	Y	ASYNC	Internal Node DX to Port Y
(Notes 2, 3)	H (Note 1)	⎍	(Note 3)	(Note 3)	SYNC	(Note 3)

Note 1: Low to High transitions of MODE__SC must be immediately preceeded by a low to high transition (clock edge) on CP__IN while holding Synchronous Control Inputs YSEL steady to preset internal registers and assure predictable operation during the control mode change from asynchronous to synchronous.

Note 2: YSEL levels are synchronously asserted by the positive transition of CP__IN when MODE__SC is high.

Note 3: Synchronous Control Mode Functions are same as Asynchronous at time T + 1 of CP__IN.

Logic Diagrams

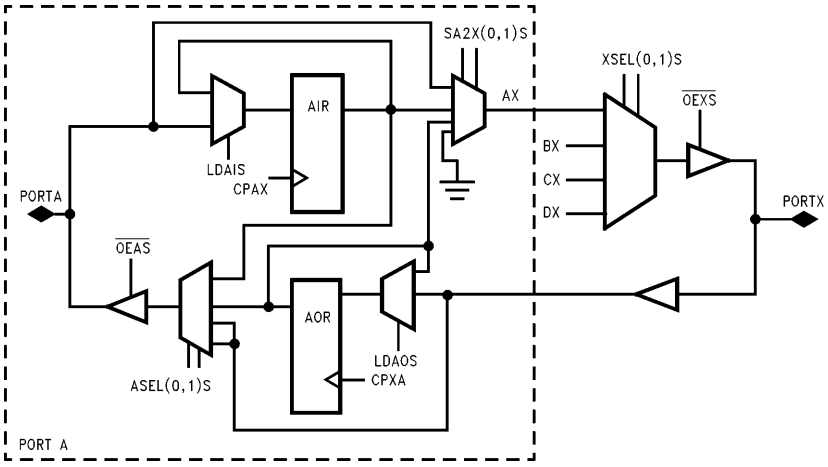


TL/F/11582–2

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

FIGURE 1. 18-Bit Synchronous Datapath Multiplexer

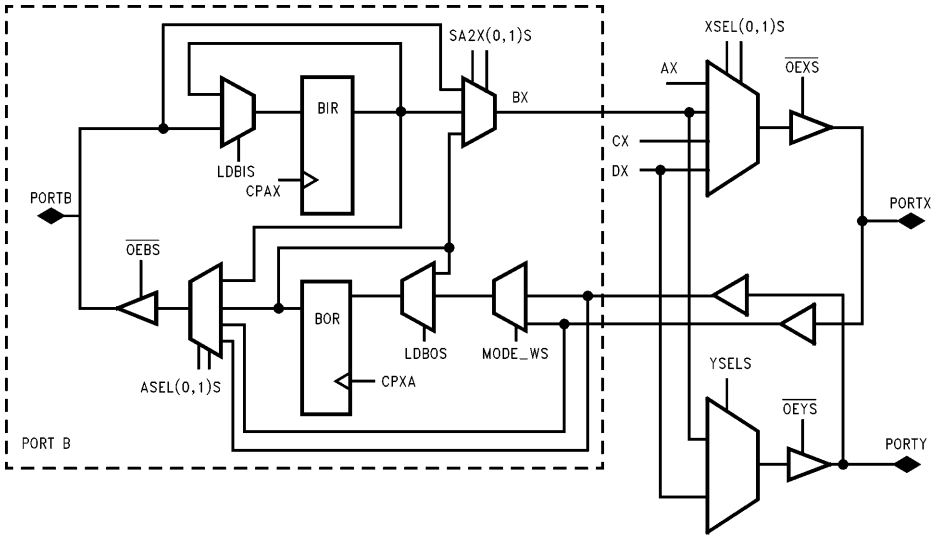
Logic Diagrams (Continued)



Note: Port C configured identical to Port A.

TL/F/11582–3

FIGURE 2. Synchronous Bus Multiplexer A-X Datapath



Note: Port D configured identical to Port B.

TL/F/11582–4

FIGURE 3. Synchronous Bus Multiplexer B PORT Datapath

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	
Ceramic	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or Power-off State	−0.5V to +5.5V
in the HIGH STATE	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−300 mA
Over Voltage Latchup (I/O)	10V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	−40°C to +85°C
Supply Voltage	
Commercial	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

DC Electrical Characteristics

Symbol	Parameter	ABT3284			Units	V_{CC}	Conditions
		Min	Typ	Max			
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.5 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −32 mA (Note 3)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA (Note 4)
I_{IH}	Input HIGH Current			5	μA	Max	V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V_{IN} = 7.0V Control Inputs
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μA	Max	V_{IN} = 5.5V (A_n, B_n, C_n, D_n, X_n, Y_n)
I_{IL}	Input LOW Current			−5	μA	Max	V_{IN} = 0.5V Control Inputs
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 μA Control Inputs All Data Pins Grounded
I_{IH} + I_{OZH}	Output Leakage Current			50	μA	0–5.5	V_{OUT} = 2.7V (A_n, B_n, C_n, D_n, X_n, Y_n) All Output Enables = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current			−50	μA	0–5.5	V_{OUT} = 0.5V (A_n, B_n, C_n, D_n, X_n, Y_n) All Output Enables = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0.0V (A_n, B_n, C_n, D_n, X_n, Y_n) (Note 5)
I_{CEX}	Output High Leakage Current			50	μA	Max	V_{OUT} = V_{CC} (A_n, B_n, C_n, D_n, X_n, Y_n)
I_{ZZ}	Bus Drainage Test			100	μA	0.0	V_{OUT} = 5.5V (A_n, B_n, C_n, D_n, X_n, Y_n)
I_{CCH}	Power Supply Current			2.5	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			140	mA	Max	36 Outputs LOW
I_{CCZ}	Power Supply Current			2.5	mA	Max	Output Enables = V_{CC}; All Others at GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_{IN} = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load			0.35	mA/ MHz	Max	Outputs Open, Transparent Mode Output Enables = GND One Bit Toggling, 50% Duty Cycle

Note 3: Up to 18 outputs can each source 32 mA continuously, or any combination of outputs can source up to a total of 324 mA. For example, 36 outputs can continuously each source 16 mA.

Note 4: Up to 18 outputs can each sink 64 mA continuously, or any combination of outputs can sink up to a total of 648 mA. For example, 36 outputs can continuously each sink 32 mA.

Note 5: One output at a time, duration 1 second maximum.

DC Electrical Characteristics (Continued)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	$T_A = 25°C$ (Note 1)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−0.8	−0.5		V	5.0	$T_A = 25°C$ (Note 1)
V_{OHV}	Minimum High Level Dynamic Output Voltage	2.5	3.0		V	5.0	$T_A = 25°C$ (Note 3)
V_{IHD}	Minimum High Level Dynamic Input Voltage	2.0	1.7		V	5.0	$T_A = 25°C$ (Note 2)
V_{ILD}	Maximum Low Level Dynamic Input Voltage		1.2	0.8	V	5.0	$T_A = 25°C$ (Note 2)

Note 1: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 2: Max number of data inputs (n) switching. n − 1 inputs switching 0V to 3V. Input-under-test switching: 3V to theshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 3: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics Single Output Switching

Symbol	Parameter	74ABT $T_A = 25°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		74ABT $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$pF		Units
		Min	Max	Min	Max	
f_{MAX}	Max Operating Frequency	150				
t_{PHL} t_{PLH}	Propagation Delay A, B, C, D or X Inputs to X or A, B, C, D Outputs. Transparent Mode	1.5	5.5	1.5	5.5	ns
t_{PHL} t_{PLH}	Propagation Delay B, D or Y Inputs to Y or B, D Outputs. Transparent Mode	1.0	5.0	1.0	5.0	ns
t_{PHL} t_{PLH}	Propagation Delay CP__XA ↑ to A, B, C, or D. Registered Mode	1.5	6.0	1.5	6.0	ns
t_{PHL} t_{PLH}	Propagation Delay CP__AX ↑ to X. Registered Mode	1.5	7.0	1.5	7.0	ns
t_{PHL} t_{PLH}	Propagation Delay CP__AX ↑ to Y. Registered Mode	1.5	6.5	1.5	6.5	ns
t_{PHL} t_{PLH}	Propagation Delay ASELn to A, B, C or D. Asynchronous Mode	2.0	7.5	2.0	7.5	ns
t_{PHL} t_{PLH}	Propagation Delay CP__IN ↑ to A, B, C or D. ASELn Synchronous Mode	2.5	8.5	2.5	8.5	ns
t_{PHL} t_{PLH}	Propagation Delay SA2Xn to X or Y. Asynchronous Mode	1.5	7.5	1.5	7.5	ns
t_{PHL} t_{PLH}	Propagation Delay CP__IN ↑ to X or Y. SA2Xn Synchronous Mode	2.0	8.5	2.0	8.5	ns
t_{PHL} t_{PLH}	Propagation Delay XSELn to X. Asynchronous Mode	1.5	6.0	1.5	6.0	ns
t_{PHL} t_{PLH}	Propagation Delay CP__IN ↑ to X. XSELn Synchronous Mode	2.0	7.5	2.0	7.5	ns
t_{PHL} t_{PLH}	Propagation Delay YSELn to Y. Asynchronous Mode	1.0	5.5	1.0	5.5	ns
t_{PHL} t_{PLH}	Propagation Delay CP__IN ↑ to Y. YSELn Synchronous Mode	1.5	6.5	1.5	6.5	ns
t_{PZH} t_{PZL}	Asynchronous Enable Time	1.0	6.0	1.0	6.0	ns
t_{PZH} t_{PZL}	Synchronous Enable Time	1.5	7.0	1.5	7.0	ns
t_{PHZ} t_{PLZ}	Asynchronous Disable Time	1.0	7.5	1.0	7.5	ns
t_{PHZ} t_{PLZ}	Synchronous Disable Time	1.5	8.5	1.5	8.5	ns

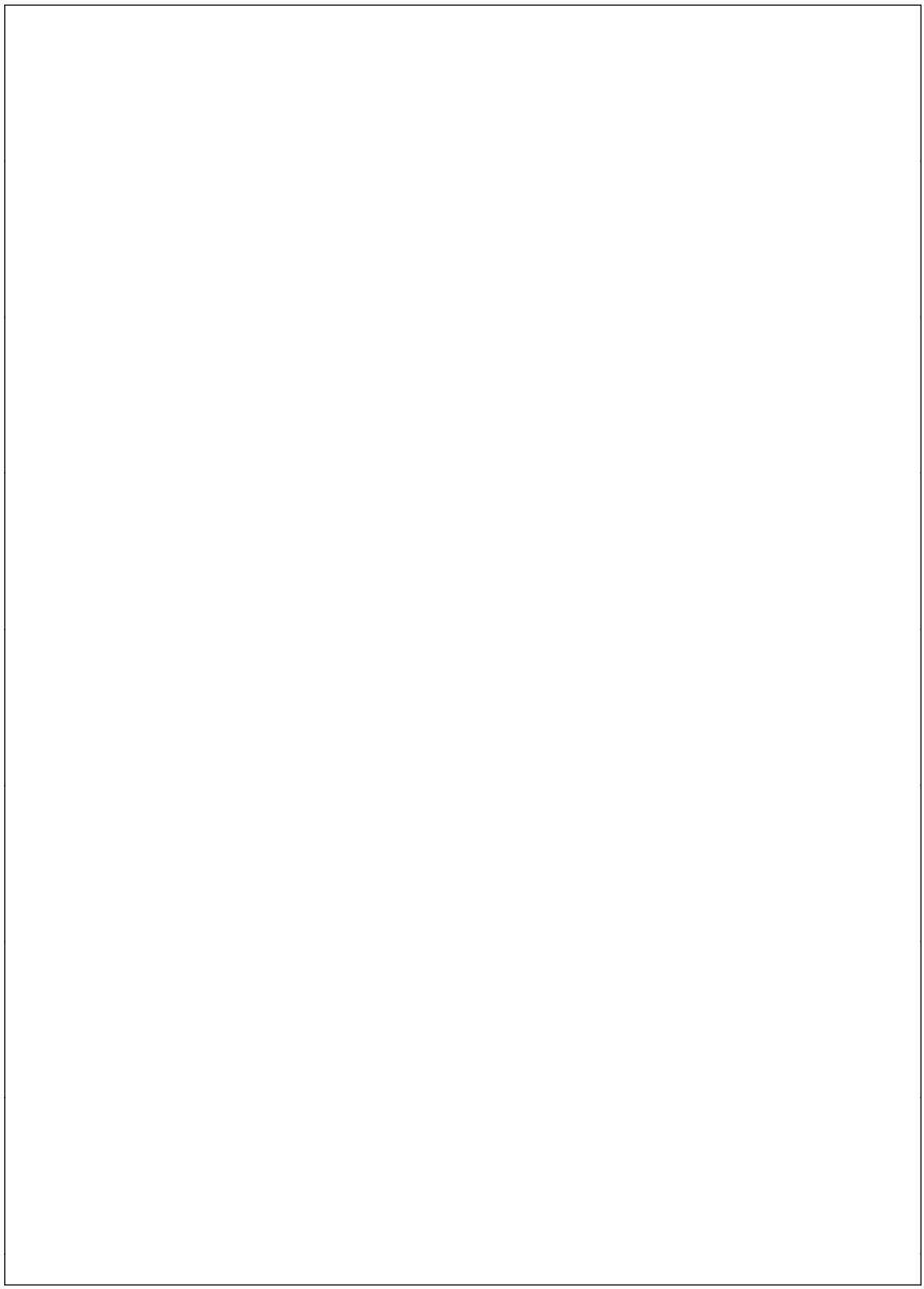
AC Operating Requirements Single Output Switching

Symbol	Parameter	74ABT $T_A = 25°C$ $V_{CC} = 5.0V$ $C_L = 50$ pF	74ABT $T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V$ to $5.5V$ $C_L = 50$ pF	Units
		Min	Max	
$t_s(H)$ $t_s(L)$	Setup Time High or Low A, B, C, D X or Y. Data to CP__AX ↑ or CP__XA ↑ (Registered Mode)	4.0	4.0	ns
$t_h(H)$ $t_h(L)$	Hold Time High or Low A, B, C, D X or Y. Data to CP__AX ↑ or CP__XA ↑ (Registered Mode)	0.0	0.0	ns
$t_s(H)$ $t_s(L)$	Setup Time High or Low Control Inputs to CP__IN ↑. (Synchronous Mode)	3.0	3.0	ns
$t_h(H)$ $t_h(L)$	Hold Time High or Low Control Inputs to CP__IN ↑. (Synchronous Mode)	0.0	0.0	ns
$t_s(H)$	Setup Time High, CP__IN ↑ to CP__AX ↑ or CP__XA ↑.	5.0	5.0	ns
$t_h(L)$	Hold Time Low, CP__IN ↑ to CP__AX ↑ or CP__XA ↑.	0.0	0.0	ns
$t_w(H)$ $t_w(L)$	CLK Pulsewidth High CLK Pulsewidth Low	3.0 4.0	3.0 4.0	ns

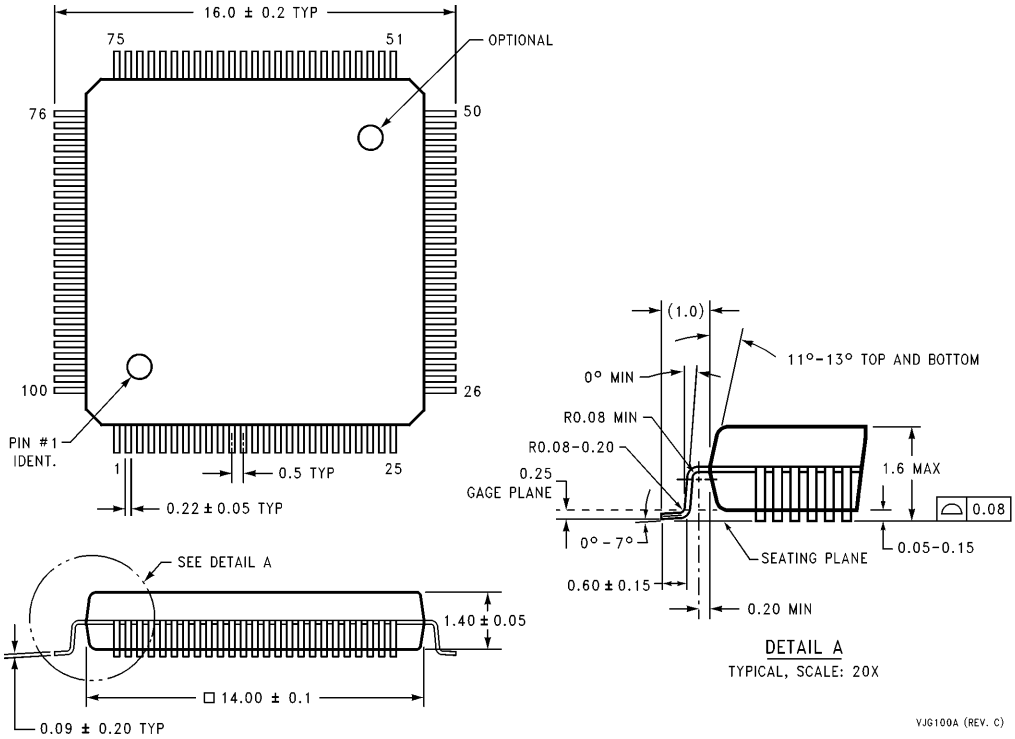
Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$ Control Inputs
$C_{I/O}$ (Note 1)	I/O Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n, C_n, D_n, X_n, Y_n)

Note 1: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.



Physical Dimensions inches (millimeters)



100-Lead Thin Quad Flatpak (TQFP)
NS Package Number VJG100A

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FAIRCHILD SEMICONDUCTOR™

January 1993
Revised November 1999

74ABT373
Octal Transparent Latch with 3-STATE Outputs

General Description

The ABT373 consists of eight latches with 3-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

Features

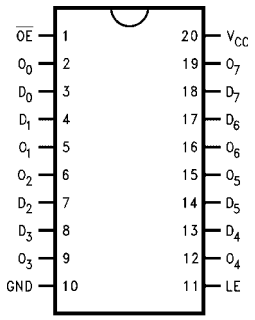
- 3-STATE outputs for bus interfacing
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT373CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT373CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT373CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT373CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT373CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input (Active HIGH)
$\overline{OE}$	Output Enable Input (Active LOW)
O_0–O_7	3-STATE Latch Outputs

Functional Description

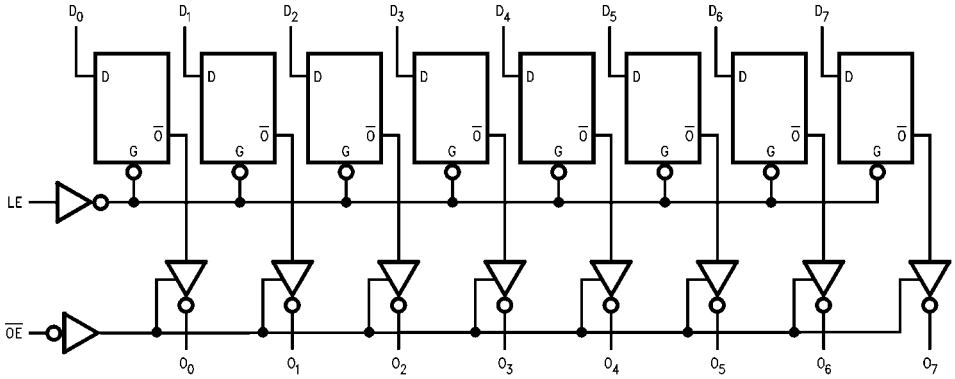
The ABT373 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Output
LE	**$\overline{OE}$**	**D_n**	**O_n**
H	L	H	H
H	L	L	L
L	L	X	O_n (no change)
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance State

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current:	$\overline{OE}$ Pin −150 mA
(Across Comm Operating Range)	Other Pins −500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1 1	μA	Max	V_{IN} = 2.7V (Note 4) V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1 −1	μA	Max	V_{IN} = 0.5V (Note 4) V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 4)	No Load			0.12	mA/ MHz	Max	Outputs Open, LE = V_{CC} $\overline{OE}$ = GND, (Note 3) One Bit Toggling, 50% Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.4	0.8	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.2	–0.8		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.7		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		0.9	0.6	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at Low. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Packages)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.9	2.7	4.5	1.0	6.8	1.9	4.5	ns
t_{PHL}	D_n to O_n	1.9	2.8	4.5	1.0	7.0	1.9	4.5	
t_{PLH}	Propagation Delay	2.0	3.1	5.0	1.0	7.7	2.0	5.0	ns
t_{PHL}	LE to O_n	2.0	3.0	5.0	1.5	7.7	2.0	5.0	
t_{PZH}	Output Enable Time	1.5	3.1	5.3	1.0	6.7	1.5	5.3	ns
t_{PZL}		1.5	3.1	5.3	1.5	7.2	1.5	5.3	
t_{PHZ}	Output Disable Time	2.0	3.6	5.4	1.7	8.0	2.0	5.4	ns
t_{PLZ}		2.0	3.4	5.4	1.0	7.0	2.0	5.4	

AC Operating Requirements

(SOIC and SSOP Packages)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100		100				MHz
t_S(H)	Setup Time, HIGH	1.5			2.5		1.5		ns
t_S(L)	or LOW D_n to LE	1.5			2.5		1.5		
t_H(H)	Hold Time, HIGH	1.0			2.5		1.0		ns
t_H(L)	or LOW D_n to LE	1.0			2.5		1.0		
t_W(H)	Pulse Width, LE HIGH	3.0			3.3		3.0		ns

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 8)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF (Note 9)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 10)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.2	2.0	6.8	2.0	9.0	ns
t_{PHL}	D_n to O_n	1.5	5.2	2.0	6.8	2.0	9.0	
t_{PLH}	Propagation Delay	1.5	5.5	2.0	7.5	2.0	9.5	ns
t_{PHL}	LE to O_n	1.5	5.5	2.0	7.5	2.0	9.5	
t_{PZH}	Output Enable Time	1.5	6.2	2.0	8.0	2.0	10.5	ns
t_{PZL}		1.5	6.2	2.0	8.0	2.0	10.5	
t_{PHZ}	Output Disable Time	1.0	5.5	(Note 11)		(Note 11)		ns
t_{PZL}		1.0	5.5					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew, HL Transitions	1.0	1.5	ns
t_{OSLH} (Note 14)	Pin to Pin Skew, LH Transitions	1.0	1.5	ns
t_{PS} (Note 16)	Duty Cycle, LH–HL Skew	1.4	3.5	ns
t_{OST} (Note 14)	Pin to Pin Skew, LH/HL Transitions	1.5	3.9	ns
t_{PV} (Note 15)	Device to Device Skew, LH/HL Transitions	2.0	4.0	ns

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: Propagation delay variation is for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

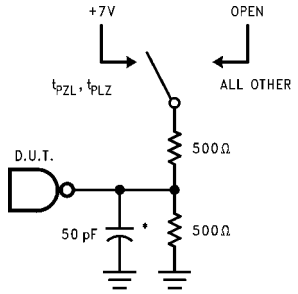
Note 16: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions ($T_A = 25°C$)
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$
C_{OUT} (Note 17)	Output Capacitance	9	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

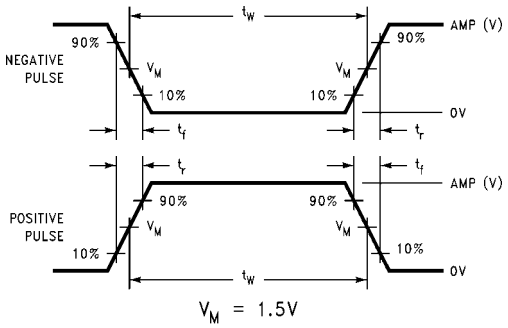


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_w	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

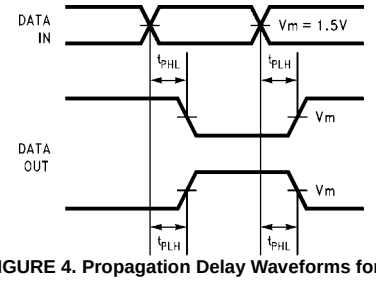


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

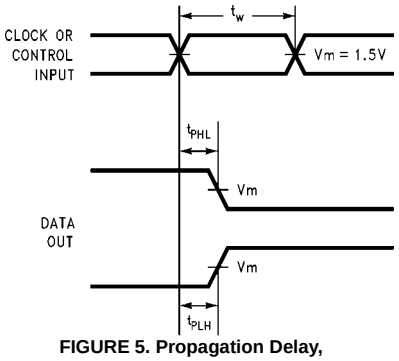


FIGURE 5. Propagation Delay, Pulse Width Waveforms

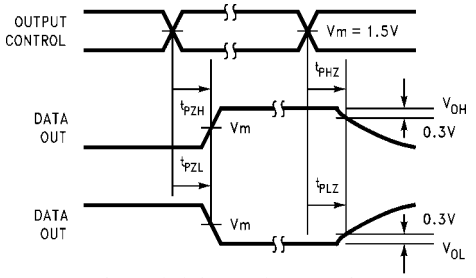


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

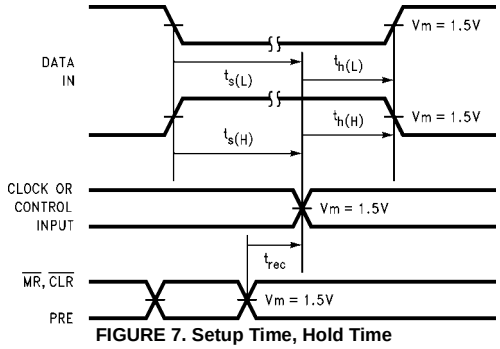
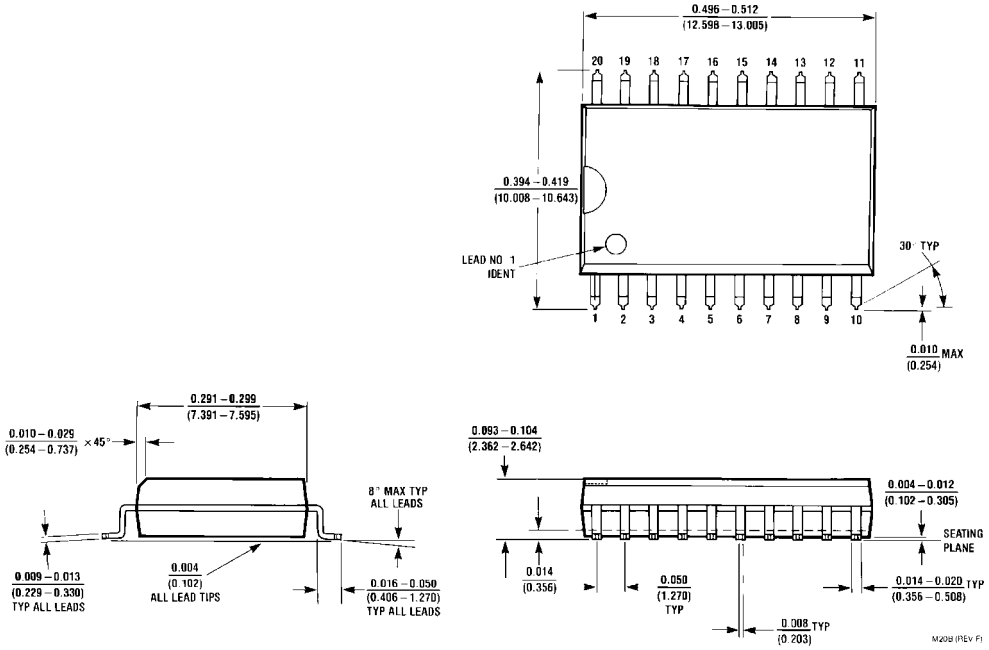


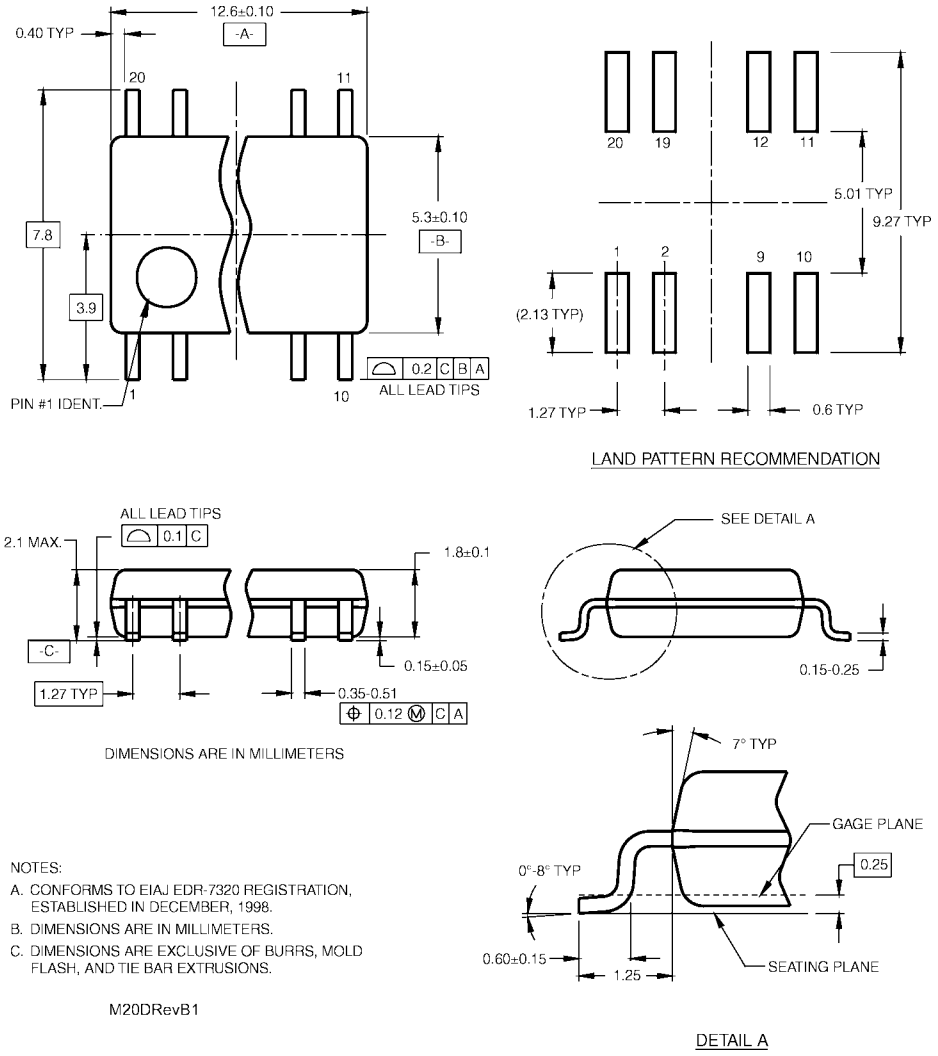
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

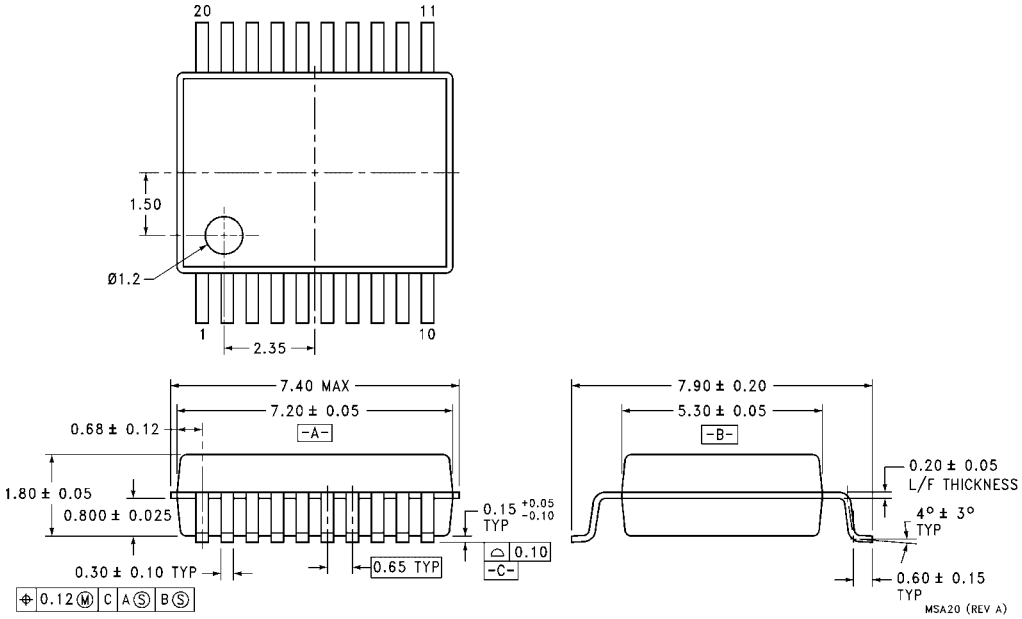
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

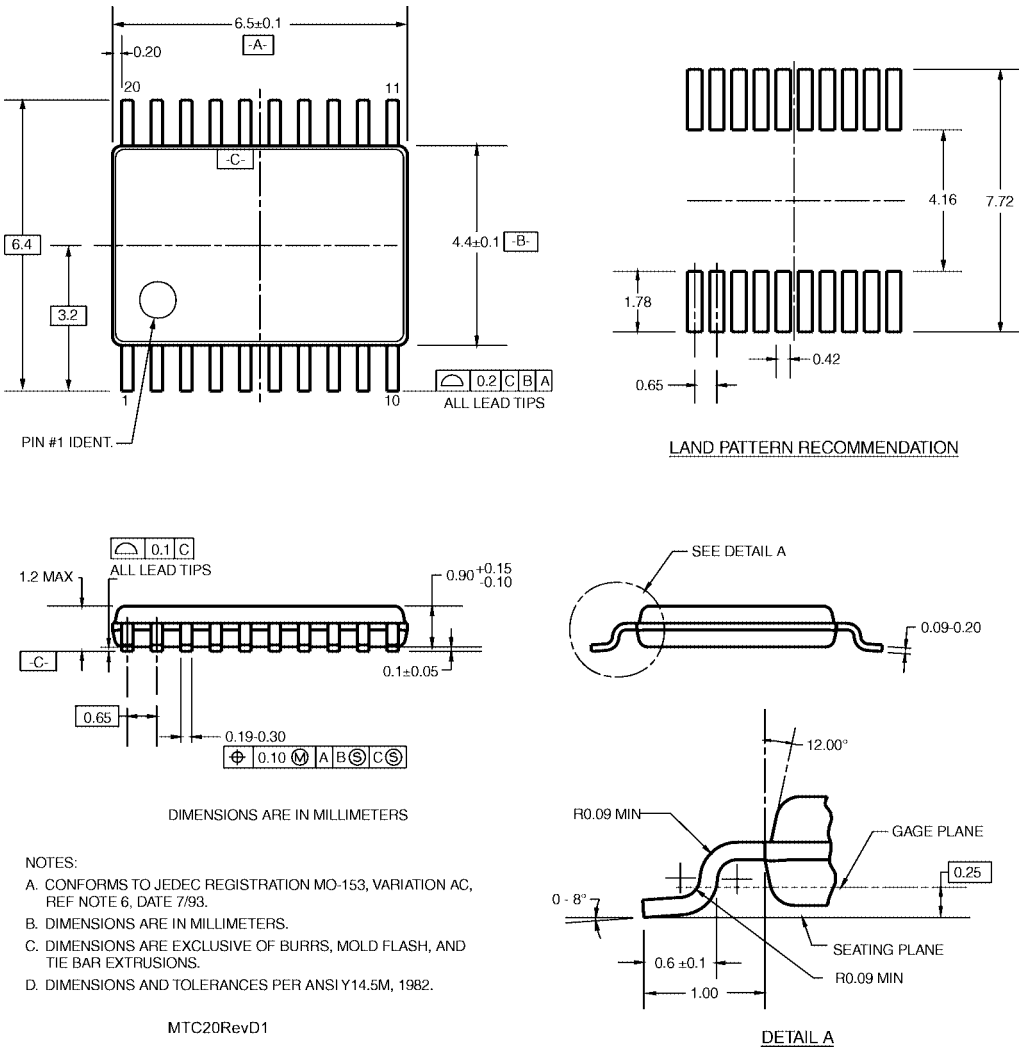
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

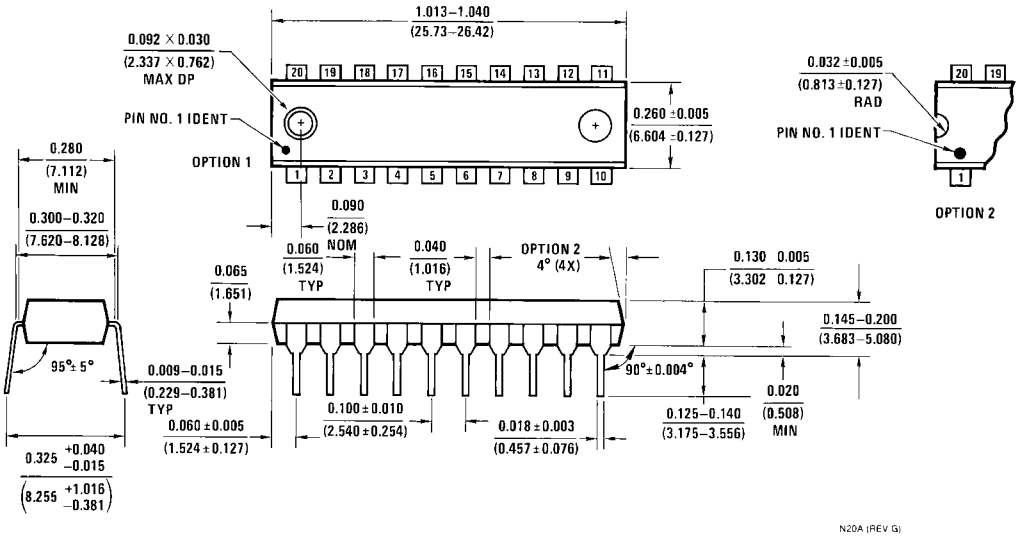
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1992
Revised November 1999

74ABT374
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The ABT374 is an octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

Features

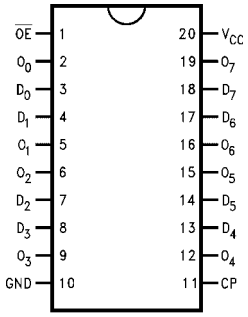
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- 3-STATE outputs for bus-oriented applications
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT374CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT374CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT374CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT374CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT374CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input (Active Rising Edge)
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)
O_0–O_7	3-STATE Outputs

Functional Description

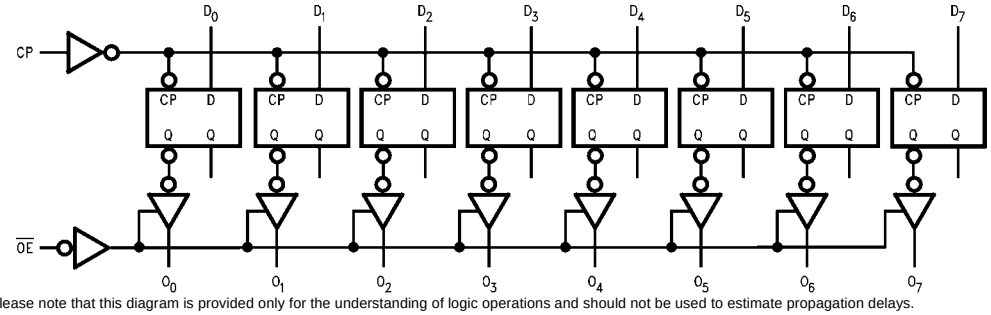
The ABT374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	⌐	L	L	Z	Load
H	⌐	H	H	Z	Load
L	⌐	L	L	L	Data Available
L	⌐	H	H	H	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disabled or Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current:	
$\overline{OE}$ Pin	−150 mA
(Across Comm Operating Range)	
Other Pins	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 4)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 4)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA, All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others V_{CC} or GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}$ = V_{CC}; All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs OPEN
	(Note 4)				0.30	MHz		$\overline{OE}$ = GND, (Note 3)
								One Bit Toggling, 50% Duty Cycle

Note 3: For 8-bit toggling, I_{CCD} <0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.5	0.8	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.3	–0.9		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.6		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.3	0.8	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at Low. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150	200		150		150		MHz
t_{PLH}	Propagation Delay	2.0	3.2	5.0	1.4	6.6	2.0	5.0	ns
t_{PHL}	CP to O_n	2.0	3.3	5.0	2.0	7.6	2.0	5.0	
t_{PZH}	Output Enable Time	1.5	3.1	5.3	0.8	5.7	1.5	5.3	ns
t_{PZL}		1.5	3.1	5.3	1.5	7.2	1.5	5.3	
t_{PHZ}	Output Disable Time	1.5	3.6	5.4	1.3	7.2	1.5	5.4	ns
t_{PLZ}		1.5	3.4	5.4	1.0	7.0	1.5	5.4	

AC Operating Requirements

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = –55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	Min	Max	
t_S(H)	Setup Time, HIGH	1.5		2.5		1.0		ns
t_S(L)	or LOW D_n to CP	1.5		2.5		1.5		
t_H(H)	Hold Time, HIGH	1.0		2.5		1.0		ns
t_H(L)	or LOW D_n to CP	1.0		2.5		1.0		
t_W(H)	Pulse Width, CP	3.0		3.3		3.0		ns
t_W(L)	HIGH or LOW	3.0		3.3		3.0		

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 8)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF (Note 9)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 10)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.7	2.0	7.8	2.0	10.0	ns
t_{PHL}	CP to O_n	1.5	5.7	2.0	7.8	2.0	10.0	
t_{PZH}	Output Enable Time	1.5	6.2	2.0	8.0	2.0	10.5	ns
t_{PZL}		1.5	6.2	2.0	8.0	2.0	10.5	
t_{PHZ}	Output Disable Time	1.0	5.5	(Note 11)		(Note 11)		ns
t_{PZL}		1.0	5.5					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delay Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew (Note 16)

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew HL Transitions	1.0	1.8	ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Transitions	1.0	1.8	ns
t_{PS} (Note 13)	Duty Cycle LH–HL Skew	1.8	4.3	ns
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Transitions	2.0	4.3	ns
t_{PV} (Note 15)	Device to Device Skew LH/HL Transitions	2.5	4.6	ns

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

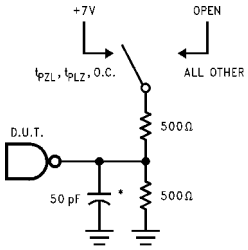
Note 16: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Capacitance

Symbol	Parameter	Typ	Units	Conditions ($T_A = 25°C$)
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 17)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

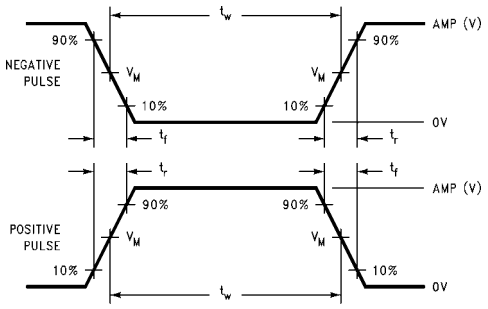


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	Rep. Rate	t_w	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

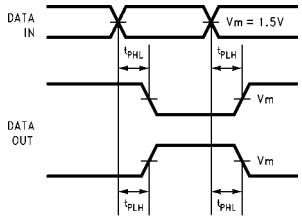


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

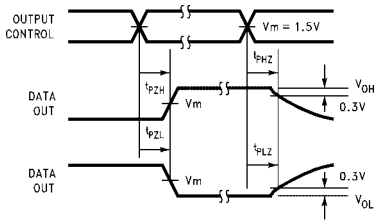


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

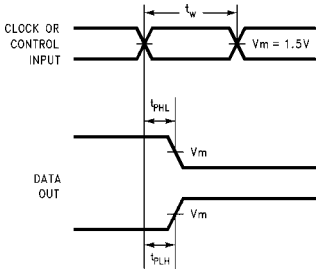


FIGURE 5. Propagation Delay, Pulse Width Waveforms

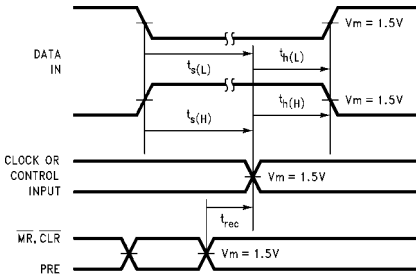
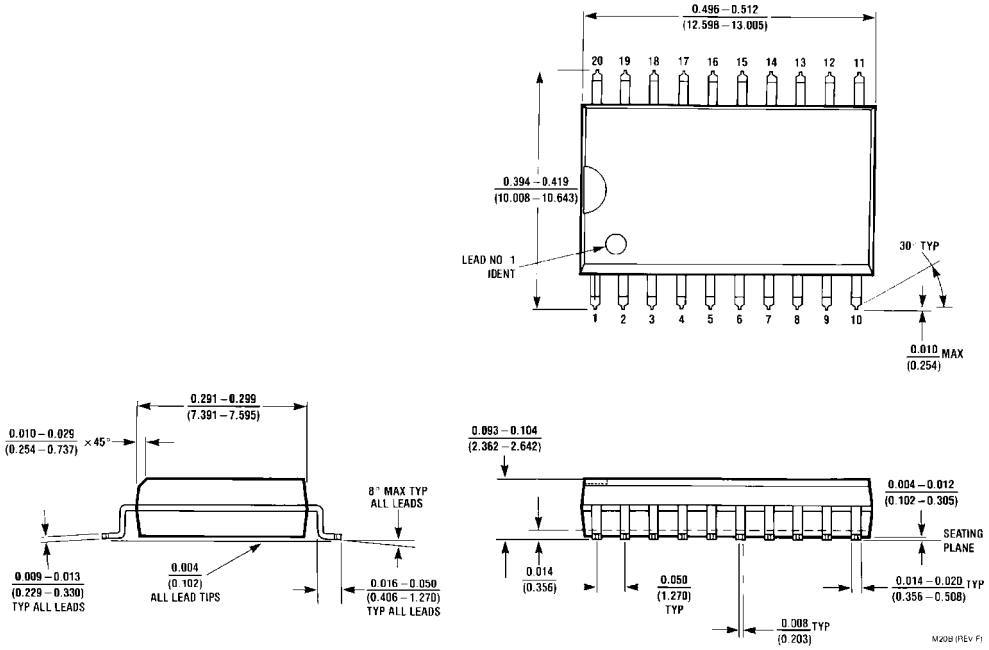


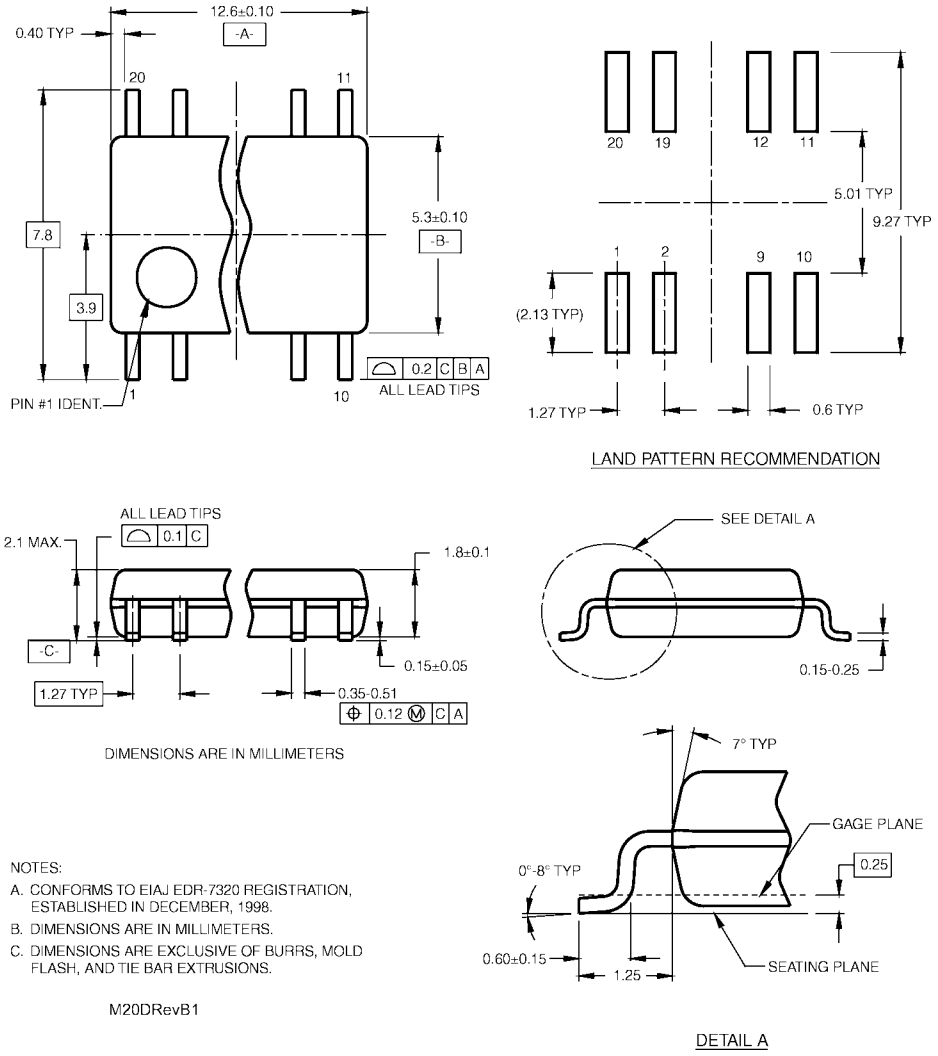
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

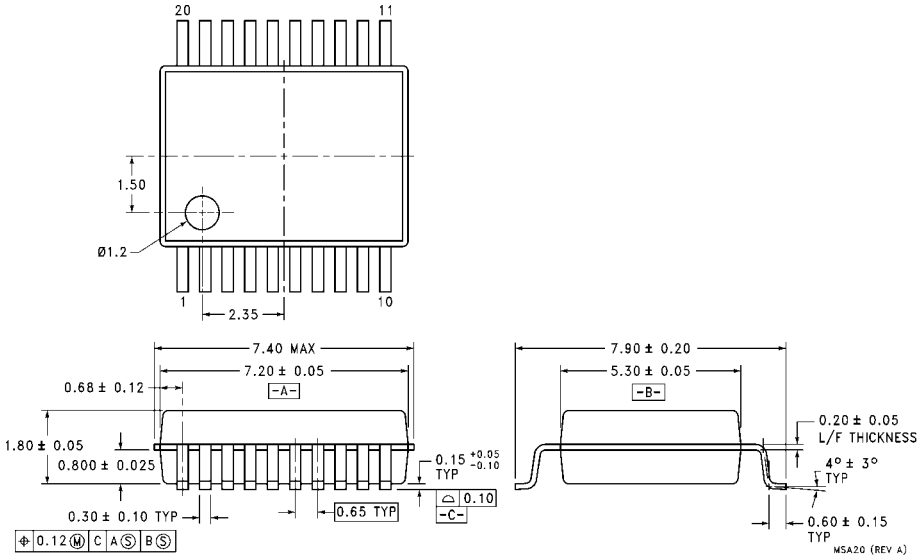
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

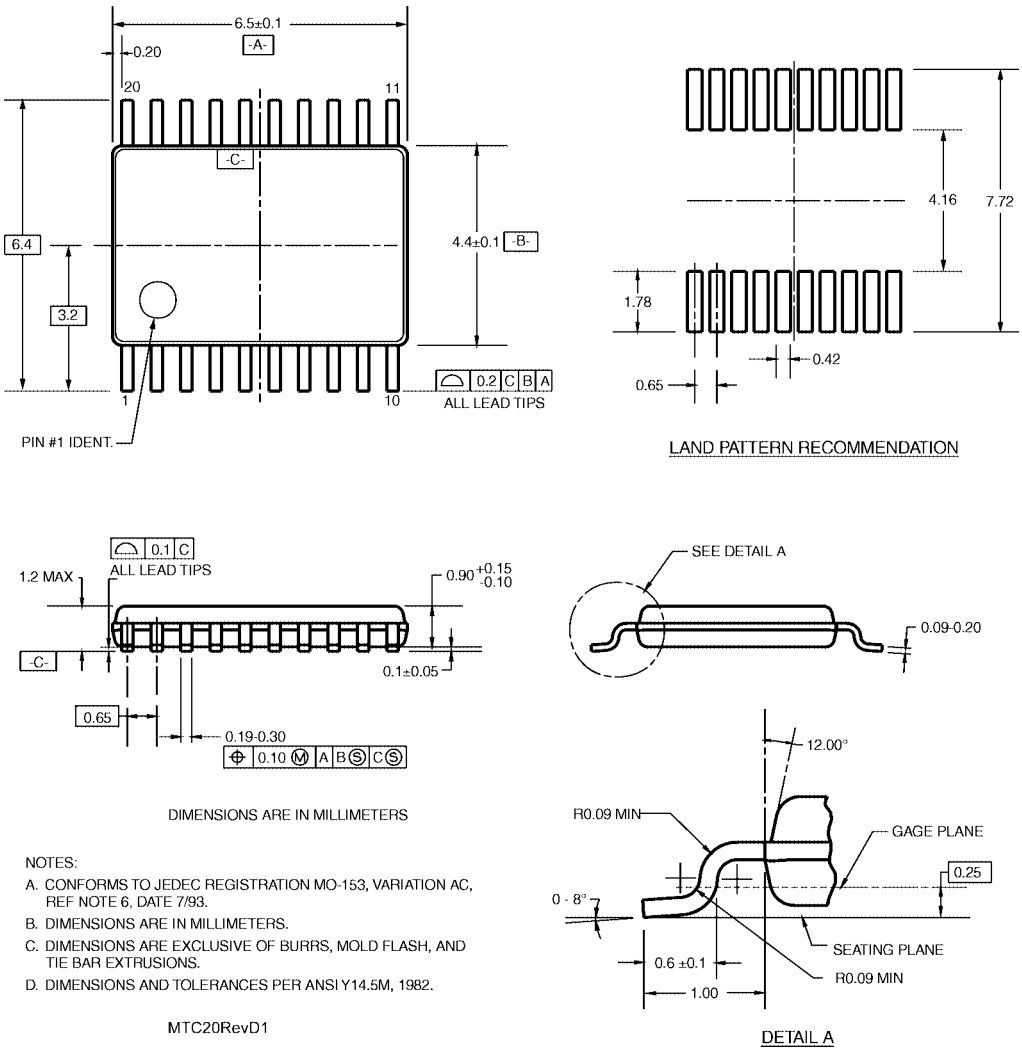
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

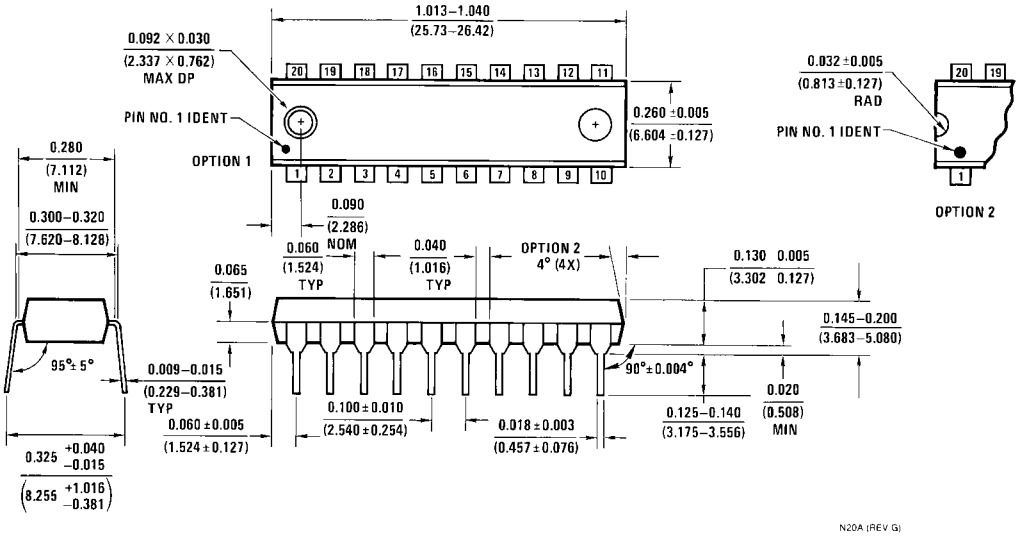
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MO-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1993
Revised November 1999

74ABT377
Octal D-Type Flip-Flop with Clock Enable

General Description

The ABT377 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) input loads all flip-flops simultaneously when the Clock Enable ($\overline{CE}$) is LOW.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output. The $\overline{CE}$ input must be stable only one setup time prior to the LOW-to-HIGH clock transition for predictable operation.

Features

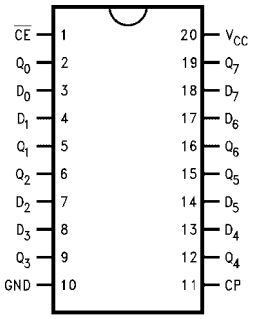
- Clock enable for address and data synchronization applications
- Eight edge-triggered D-type flip-flops
- Buffered common clock
- See ABT273 for master reset version
- See ABT373 for transparent latch version
- See ABT374 for 3-STATE version
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability
- Disable time less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT377CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT377CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT377CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT377CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

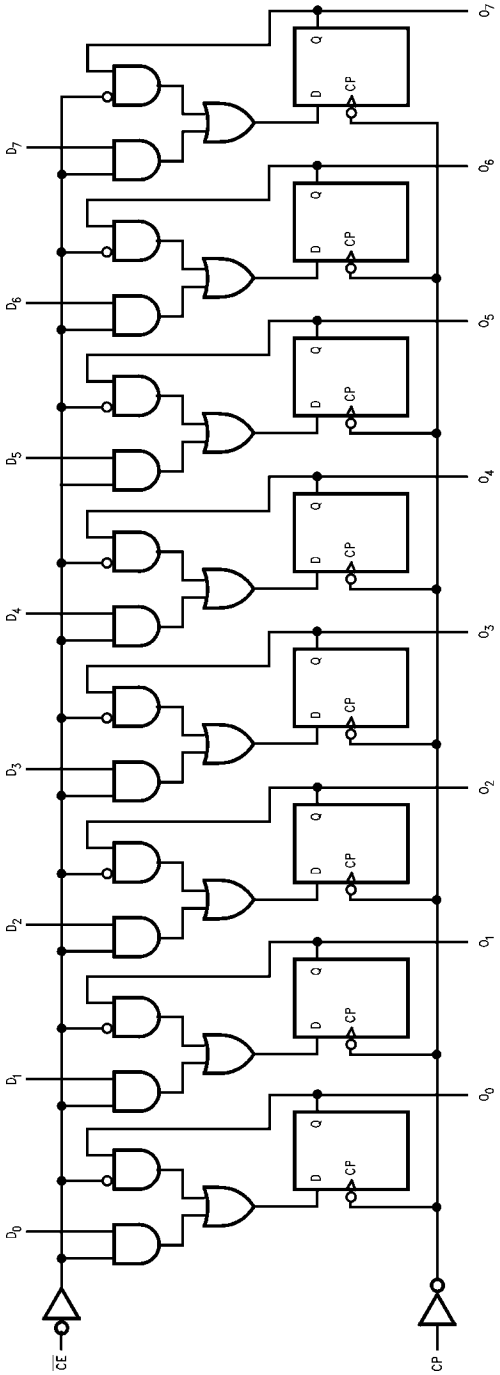
Pin Names	Descriptions
D_0–D_7	Data Inputs
$\overline{CE}$	Clock Enable (Active LOW)
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

Truth Table

Operating Mode	Inputs			Output
	CP	$\overline{CE}$	D_n	Q_n
Load "1"	⌐	l	h	H
Load "0"	⌐	l	l	L
Hold	⌐	h	X	No Change
(Do Nothing)	X	H	X	No Change

H = HIGH Voltage Level L = LOW Voltage Level
X = Immaterial ⌐ = LOW-to-HIGH Clock Transition
h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH Clock Transition
l = LOW Voltage Level one setup time prior to the LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-OFF State	−0.5V to +4.75V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	Twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
(Across Comm Operating Range)	
Over Voltage Latchup	V_{CC} + 4.5V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.5 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −32 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			1 1	μA	Max	V_{IN} = 2.7V (Note 3) V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−1 −1	μA	Max	V_{IN} = 0.5V (Note 3) V_{IN} = 0.0V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	μA	Max	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current			50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I_{CCT}	Maximum I_{CC}/Input Outputs Enabled			1.5	mA	Max	V_I = V_{CC} − 2.1V Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load			0.3	mA/ MHz	Max	Outputs Open (Note 4) One bit Toggling, 50% Duty Cycle

Note 3: Guaranteed but not tested.

Note 4: For 8 bits toggling, I_{CCD} < 0.5 mA/MHz.

AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150	200		150		MHz
t_{PLH}	Propagation Delay	2.2		6.0	2.2	6.0	ns
t_{PHL}	CP to O_n	2.8		6.8	2.8	6.8	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH	2.0		2.0		ns
$t_S(L)$	or LOW D_n to CP	2.0		2.0		
$t_H(H)$	Hold Time, HIGH	1.8		1.8		ns
$t_H(L)$	or LOW D_n to CP	1.8		1.8		
$t_S(H)$	Setup Time, HIGH	3.0		3.0		ns
$t_S(L)$	or LOW $\overline{CE}$ to CP	3.0		3.0		
$t_H(H)$	Hold Time, HIGH	1.0		1.0		ns
$t_H(L)$	or LOW $\overline{CE}$ to CP	1.0		1.0		
$t_W(H)$	Pulse Width, CP,	3.3		3.3		ns
$t_W(L)$	HIGH or LOW	3.3		3.3		

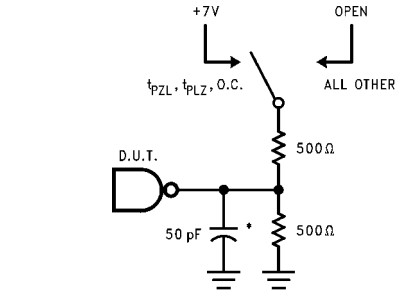
Capacitance

(SOIC Package) (Note 5)

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$, $T_A = 25°C$
C_{OUT} (Note 5)	Output Capacitance	9	pF	$V_{CC} = 5.0V$

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

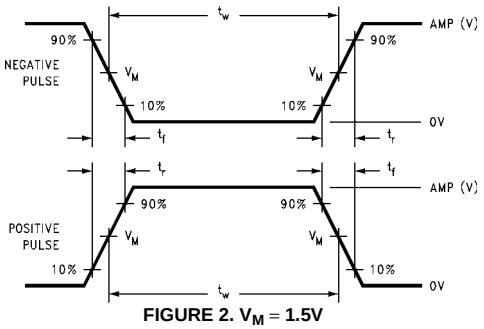


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

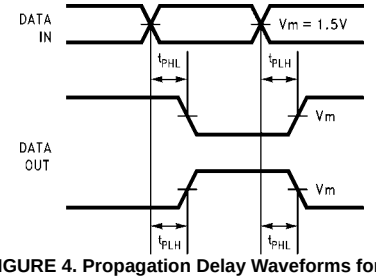


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

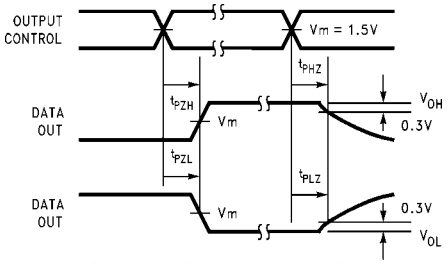


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

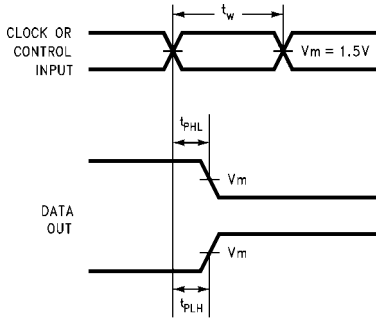


FIGURE 5. Propagation Delay, Pulse Width Waveforms

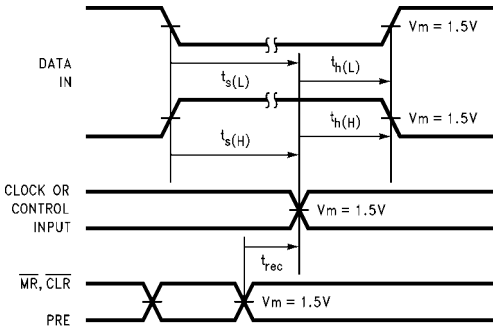
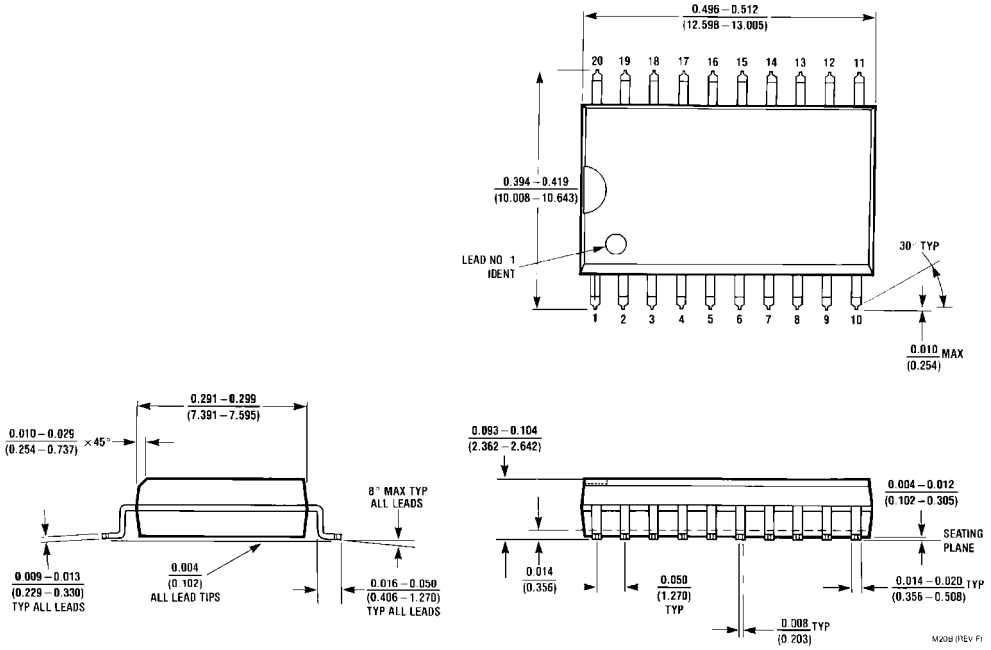


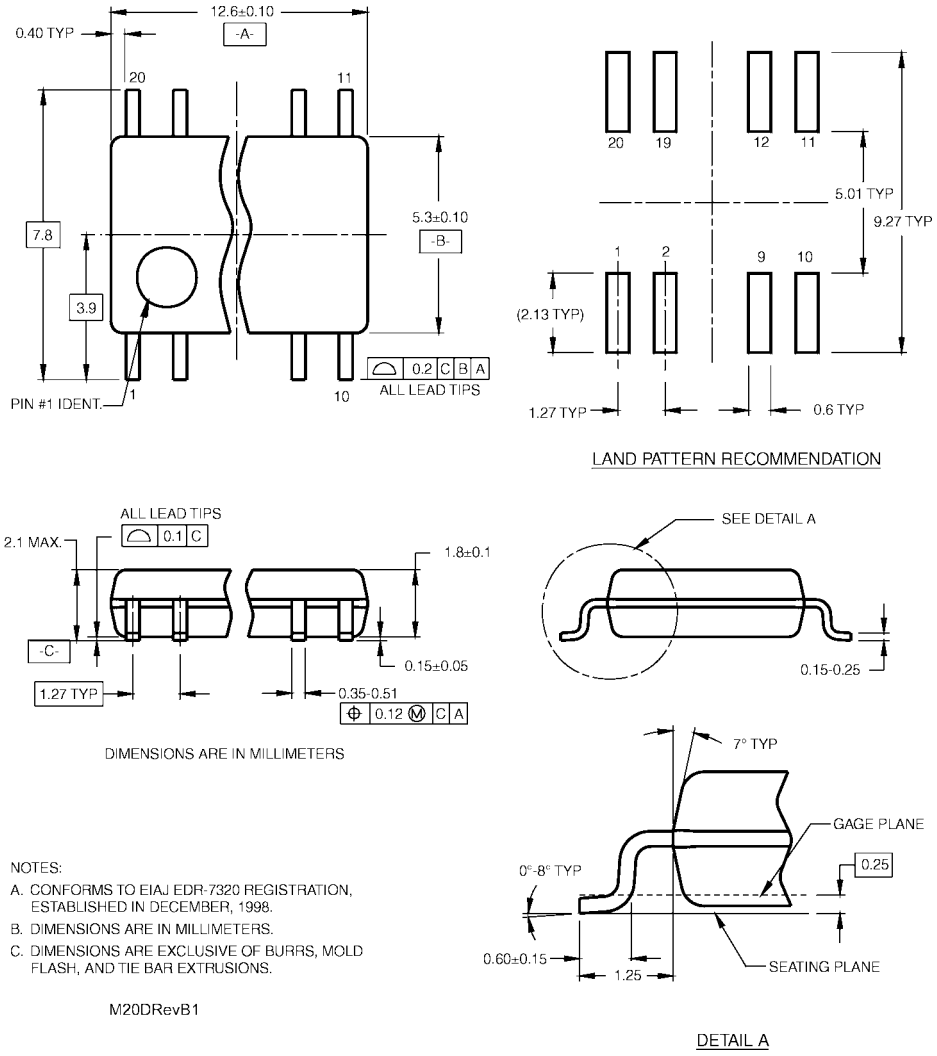
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

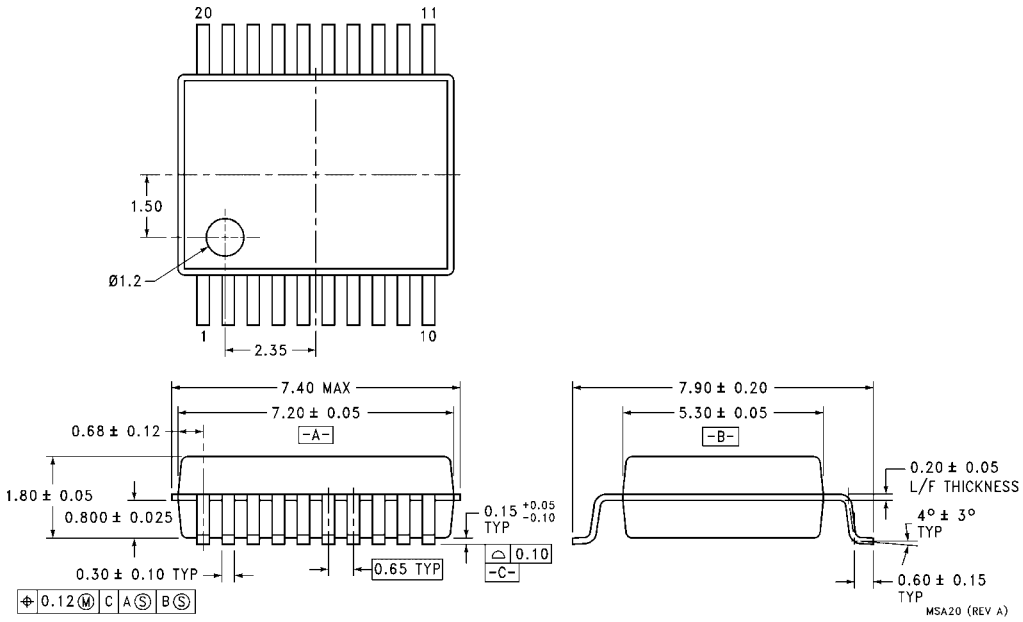
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

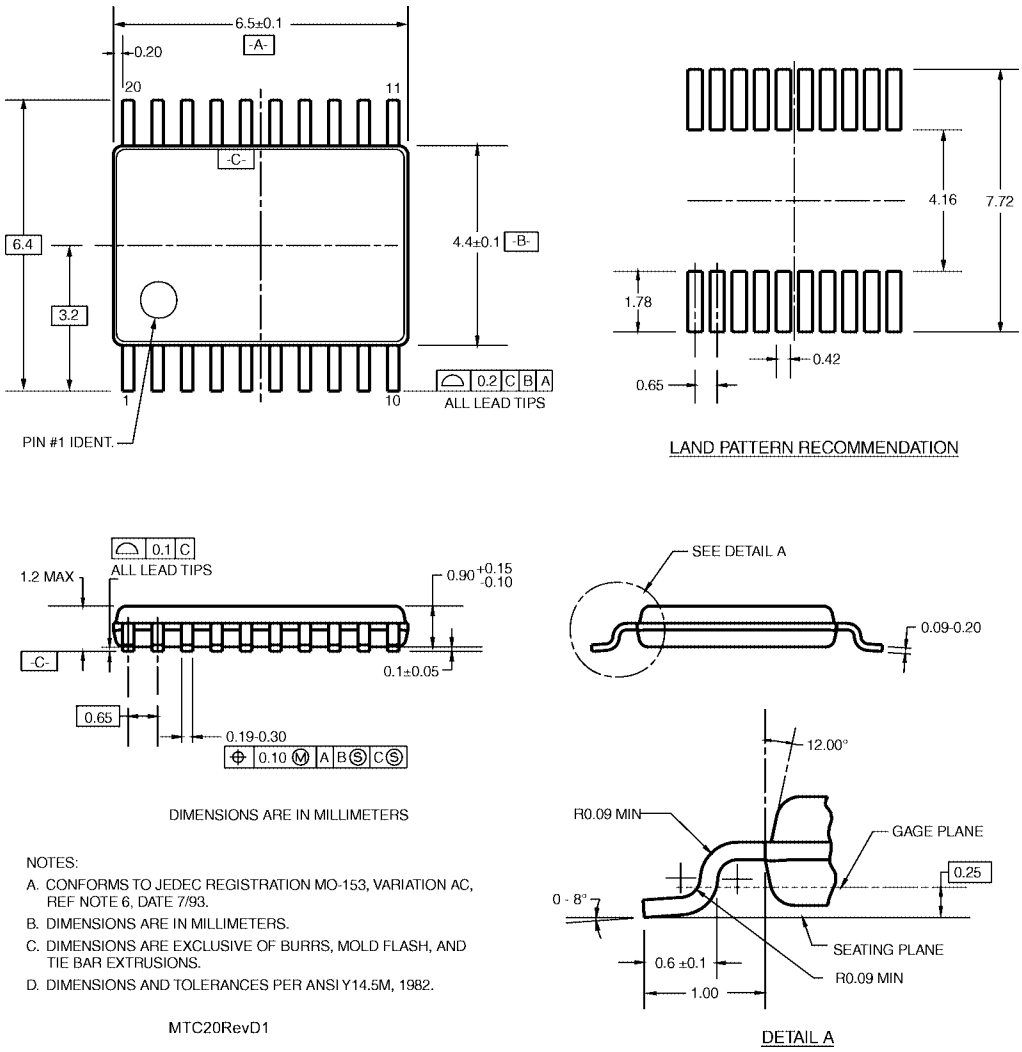
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

September 1992
Revised November 1999

74ABT541
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ABT541 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The ABT541 is similar to the ABT244 with broadside pinout.

Features

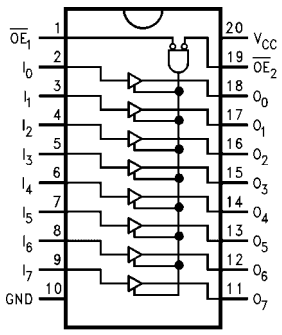
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance, glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Flow-through pinout for ease of PC board layout
- Disable time less than enable time to avoid bus contention

Ordering Code:

Order Number	Package Number	Package Description
74ABT541CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT541CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT541CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT541CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT541CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	μA	Max	V_{IN} = 2.7V (Note 4)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	μA	Max	V_{IN} = 0.5V (Note 4)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V; All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC} (Note 4)	No Load			0.1	mA/MHz	Max	Outputs Open, $\overline{OE}_n$ = GND, One Bit Toggling (Note 3), 50% Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.3	−0.8		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.4		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.1	0.6	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.0	3.6	1.0	3.6	ns
t_{PHL}	Data to Outputs	1.0	2.4	3.6	1.0	3.6	
t_{PZH}	Output Enable Time	1.5	3.1	6.0	1.5	6.0	ns
t_{PZL}		1.5	3.7	6.0	1.5	6.0	
t_{PHZ}	Output Disable Time	1.7	3.5	6.1	1.7	6.1	ns
t_{PLZ}		1.7	3.1	5.6	1.7	5.6	

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	−40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF, 8 Outputs Switching (Note 8)			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 1 Output Switching (Note 9)		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 250 pF, 8 Outputs Switching (Note 10)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.5	ns
t_{PHL}	Data to Outputs	1.5		5.0	1.5	6.0	2.5	8.5	
t_{PZH}	Output Enable Time	1.5		6.5	2.5	7.5	2.5	9.5	ns
t_{PZL}		1.5		6.5	2.5	7.5	2.5	10.5	
t_{PHZ}	Output Disable Time	1.0		6.1	(Note 11)				ns
t_{PLZ}		1.0		5.6					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew, HL Transitions	1.3	2.3	ns
t_{OSLH} (Note 14)	Pin to Pin Skew, LH Transitions	1.0	1.8	ns
t_{PS} (Note 15)	Duty Cycle, LH/HL Skew	2.0	3.5	ns
t_{OST} (Note 14)	Pin to Pin Skew, LH/HL Transitions	2.0	3.5	ns
t_{PV} (Note 16)	Device to Device Skew, LH/HL Transitions	2.0	3.5	ns

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 13: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). The specification is guaranteed but not tested.

Note 15: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Note 16: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
				$T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0.0V$
C_{OUT} (Note 17)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency of f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading

*Includes jig and probe capacitance

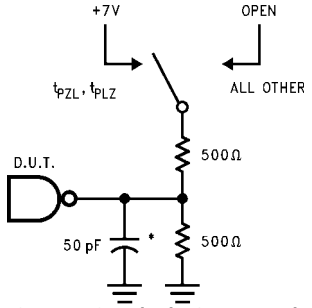


FIGURE 1. Standard AC Test Load

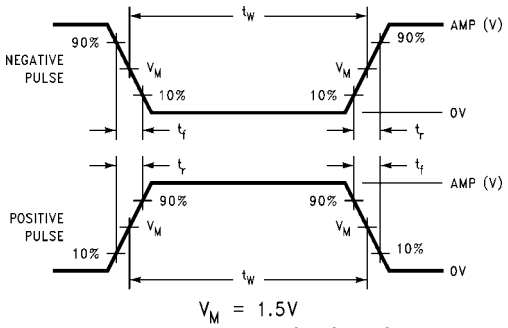


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

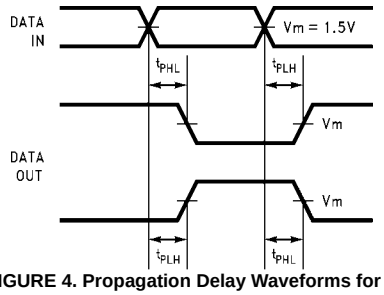


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

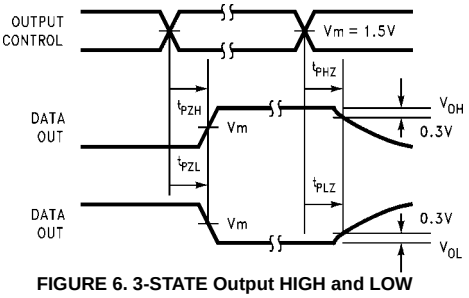


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Time

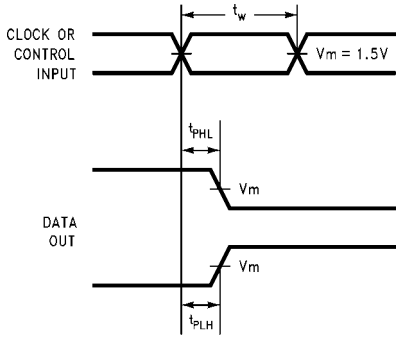


FIGURE 5. Propagation Delay, Pulse Width Waveforms

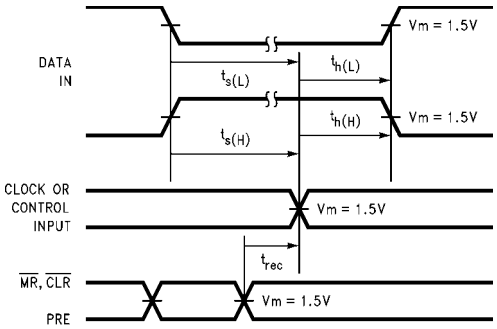
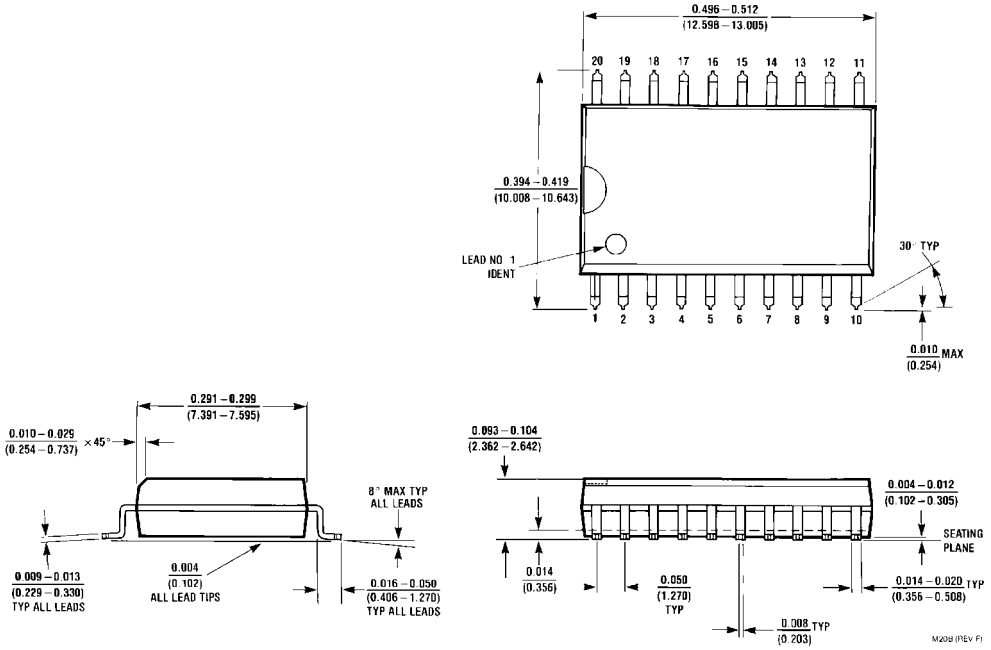


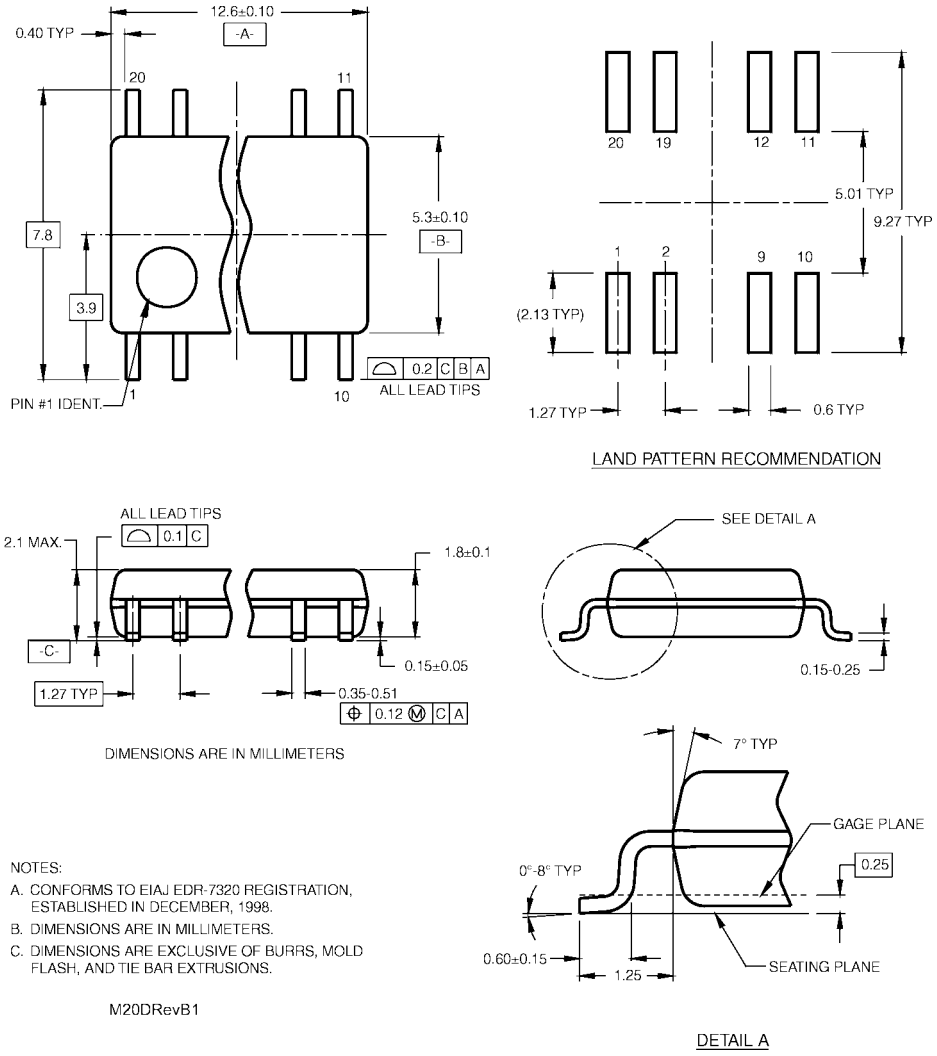
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013,0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

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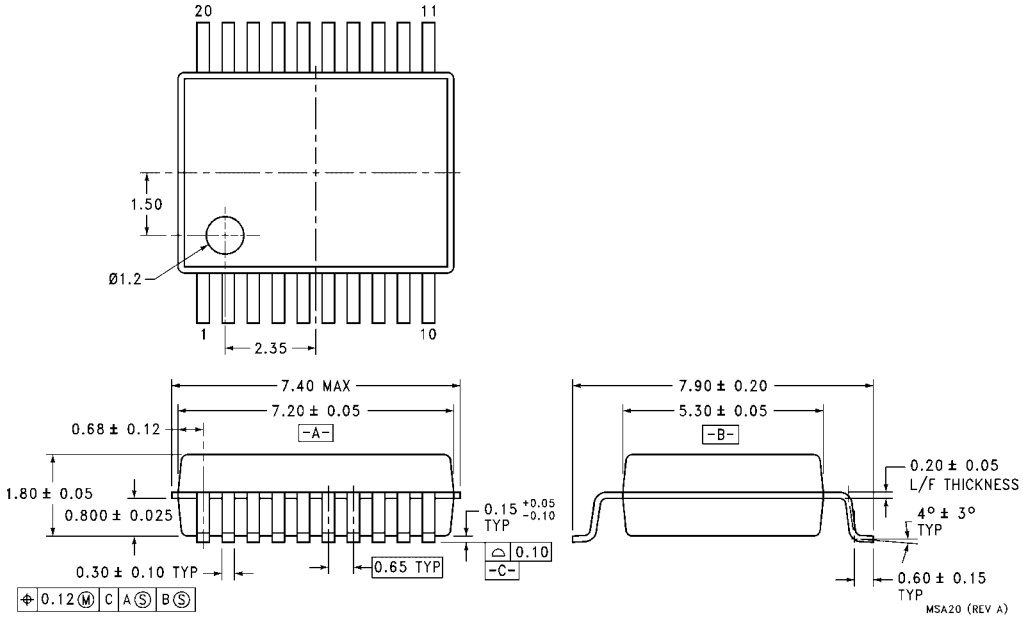
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

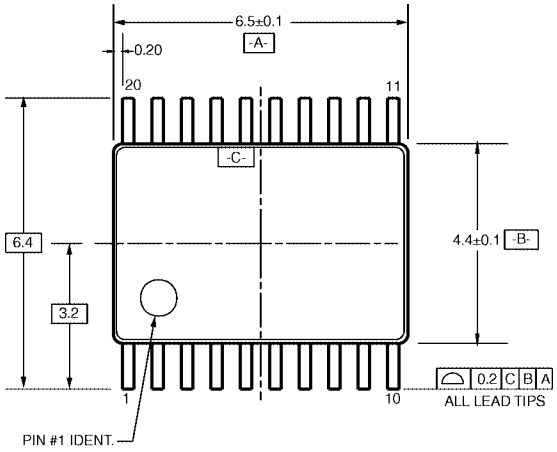
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

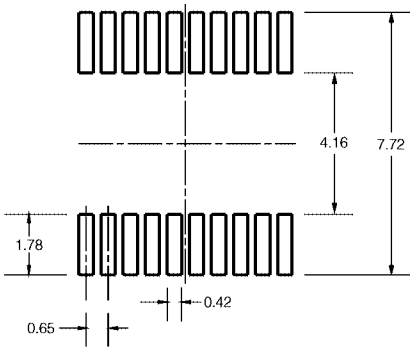
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



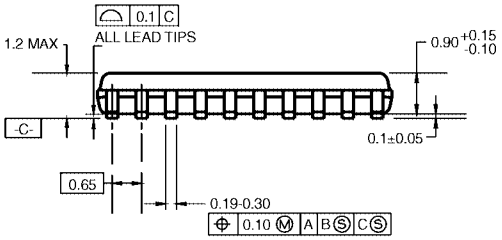
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

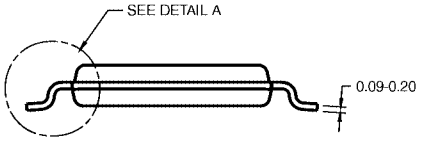
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

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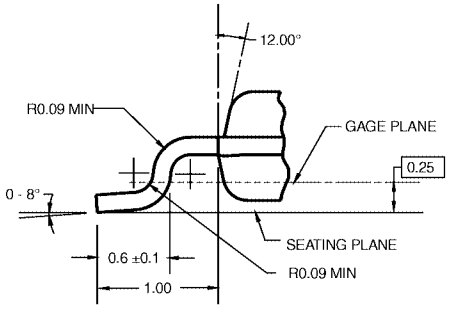
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

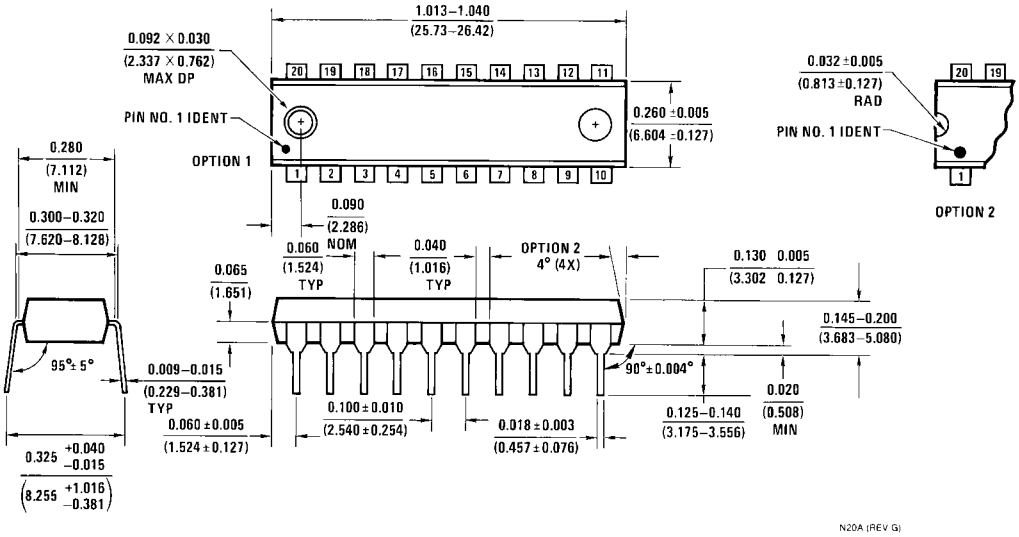
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised January 1999

74ABT543
Octal Registered Transceiver with 3-STATE Outputs

General Description

The ABT543 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow.

Features

- Back-to-back registers for storage
- Bidirectional data path
- A and B outputs have current sourcing capability of 32 mA and current sinking capability of 64 mA
- Separate controls for data flow in each direction
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

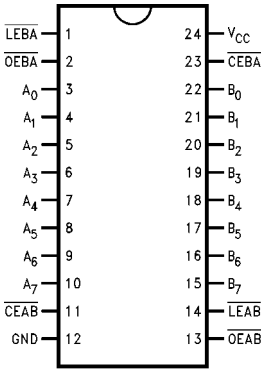
Ordering Code:

Order Number	Package Number	Package Description
74ABT543CSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT543CMSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT543CMTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for SOIC, SSOP and TSSOP



Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs
$\overline{LEAB}$, $\overline{LEBA}$	Latch Enable Inputs
$\overline{CEAB}$, $\overline{CEBA}$	Chip Enable Inputs
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Functional Description

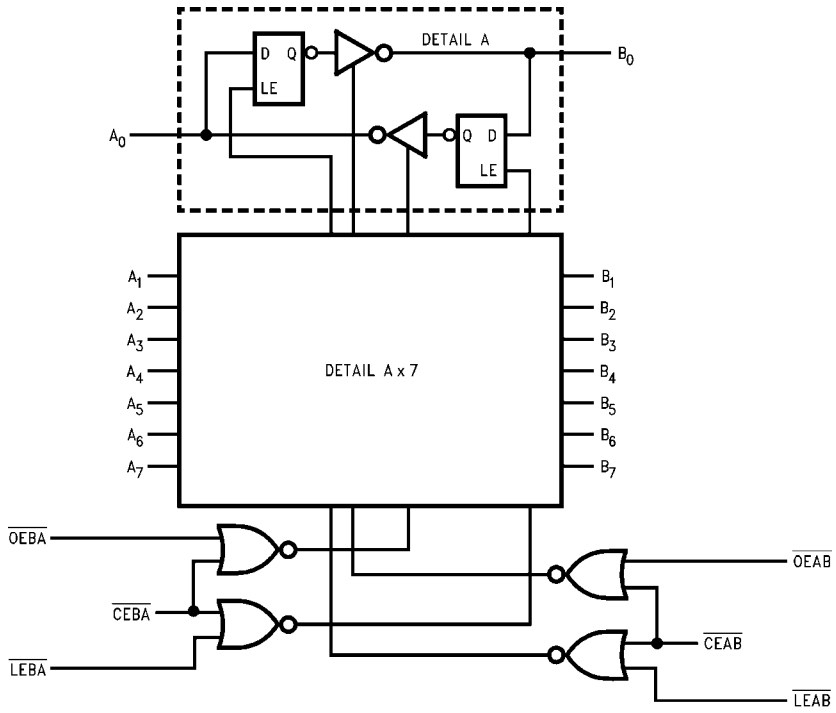
The ABT543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable ($\overline{CEAB}$) input must be low in order to enter data from the A Port or take data from the B Port as indicated in the Data I/O Control Table. With $\overline{CEAB}$ low, a low signal on ($\overline{LEAB}$) input makes the A to B latches transparent; a subsequent low to high transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both low, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$.

Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	HIGH Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	HIGH Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disable or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage	0.8			V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V		I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5					I_{OH} = −3 mA, (A_n, B_n)
		2.0					I_{OH} = −32 mA, (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA, (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins)
							All Other Pins Grounded
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 3)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 3)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OEAB}$ or $\overline{CEAB}$ = 2V
I_{IL} + I_{OZL}	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OEAB}$ or $\overline{CEAB}$ = 2V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCLH}	Power Supply Current			50	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			50	µA	Max	Outputs 3-STATE; All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V; All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 5)			0.18	mA/MHz	Max	Outputs Open, $\overline{CEAB}$ and $\overline{OEAB}$ = GND, $\overline{CEBA}$ = V_{CC}, One Bit Toggling, 50% Duty Cycle, (Note 4)

Note 3: Guaranteed but not tested.

Note 4: For 8-bit toggling. I_{CCD} < 1.4 mA/MHz.

Note 5: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	T_A = 25°C (Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.2	–0.8		V	5.0	T_A = 25°C (Note 6)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.7		V	5.0	T_A = 25°C (Note 8)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		0.7	0.9	V	5.0	T_A = 25°C (Note 8)

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 8: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Packages)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	3.1	4.8	1.5	4.8	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.5		4.8	1.5	4.8	
t_{PLH}	Propagation Delay						
t_{PHL}	$\overline{LEAB}$ to B_n, $\overline{LEBA}$ to A_n	1.6	3.4	5.3	1.6	5.3	ns
	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.6		5.3	1.6	5.3	
t_{PZH}	Enable Time						
t_{PZL}	$\overline{LEAB}$ to B_n, $\overline{LEBA}$ to A_n	1.5	3.6	5.8	1.5	5.8	ns
	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.5		5.8	1.5	5.8	
t_{PHZ}	Disable Time	2.0	4.0	6.5	2.0	6.5	ns
t_{PLZ}	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	2.0		6.5	2.0	6.5	

AC Operating Requirements

(SOIC and SSOP Packages)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	
t_S(H)	Setup Time, HIGH or LOW	1.5		1.5		ns
t_S(L)	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	1.5		1.5		
t_H(H)	Hold Time, HIGH or LOW	1.0		1.0		ns
t_H(L)	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	1.0		1.0		
t_S(H)	Setup Time, HIGH or LOW	1.5		1.5		ns
t_S(L)	A_n or B_n to $\overline{CEAB}$ or $\overline{CEBA}$	1.5		1.5		
t_H(H)	Hold Time, HIGH or LOW	1.3		1.3		ns
t_H(L)	A_n or B_n to $\overline{CEAB}$ or $\overline{CEBA}$	1.3		1.3		
t_W(L)	Pulse Width, LOW	3.0		3.0		ns

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 9)			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 10)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 11)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		6.2	2.0	7.5	2.5	10.0	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.5		6.2	2.0	7.5	2.5	10.0	
t_{PLH}	Propagation Delay	1.5		6.5	2.0	8.0	2.5	10.5	ns
t_{PHL}	$\overline{LEAB}$ to B_n, $\overline{LEBA}$ to A_n	1.5		6.5	2.0	8.0	2.5	10.5	
t_{PZH}	Output Enable Time								
t_{PZL}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.5		7.5	2.0	8.5	2.5	11.0	ns
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	1.5		7.5	2.0	8.5	2.5	11.0	
t_{PHZ}	Output Disable Time								
t_{PLZ}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.5		8.5	(Note 12)		(Note 12)		ns
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	1.5		8.5					

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delay with 250pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 12: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 13)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 14)	Units
		Max	Max	
t_{OSHL} (Note 15)	Pin to Pin Skew HL Transitions	1.0	2.0	ns
t_{OSLH} (Note 15)	Pin to Pin Skew LH Transitions	1.3	2.0	ns
t_{PS} (Note 16)	Duty Cycle LH–HL Skew	2.0	4.0	ns
t_{OST} (Note 15)	Pin to Pin Skew LH/HL Transitions	2.0	4.0	ns
t_{PV} (Note 17)	Device to Device Skew LH/HL Transitions	2.5	4.5	ns

Note 13: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 14: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 16: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

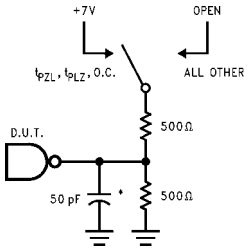
Note 17: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions: $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	V_{CC} = 0V (non I/O pins)
$C_{I/O}$ (Note 18)	Output Capacitance	11.0	pF	V_{CC} = 5.0V (A_n, B_n)

Note 18: $C_{I/O}$ is measured at frequency, f = 1 MHz, PER MLT-STD-883B, METHOD 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

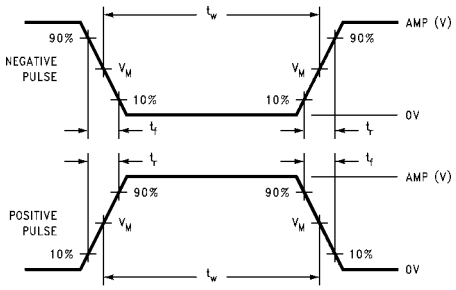


FIGURE 2. V_M = 1.5V Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

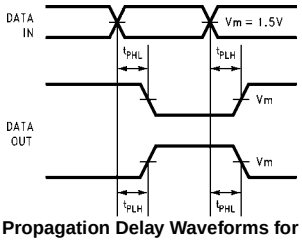


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

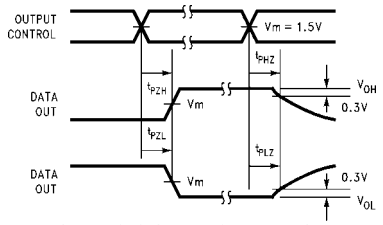


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

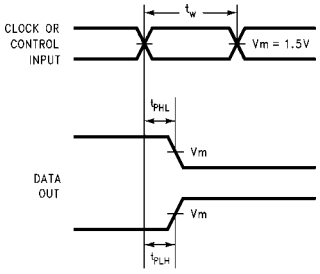


FIGURE 5. Propagation Delay, Pulse Width Waveforms

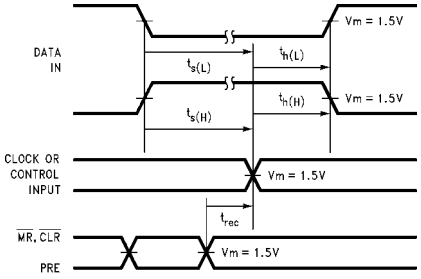
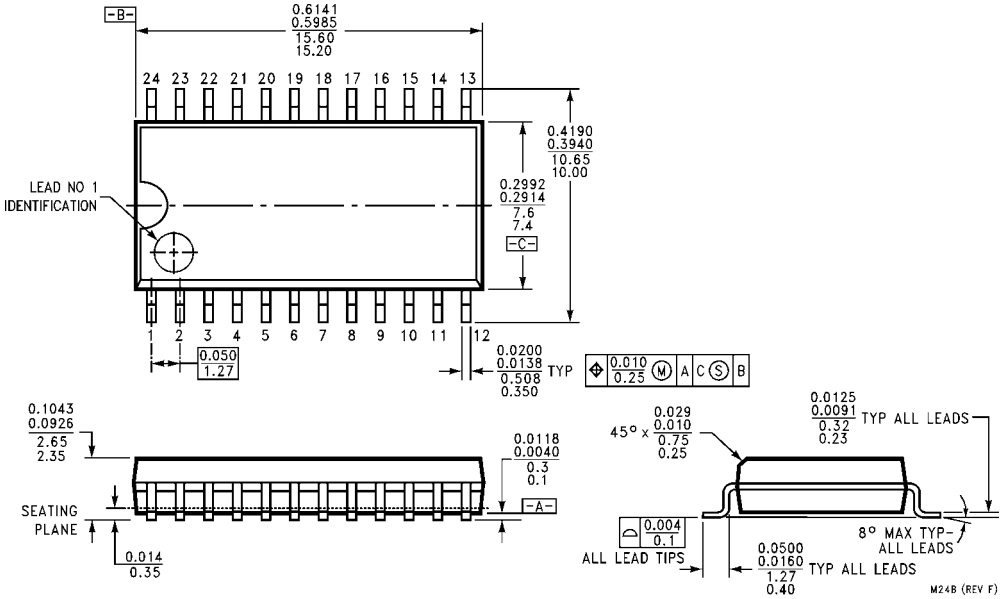
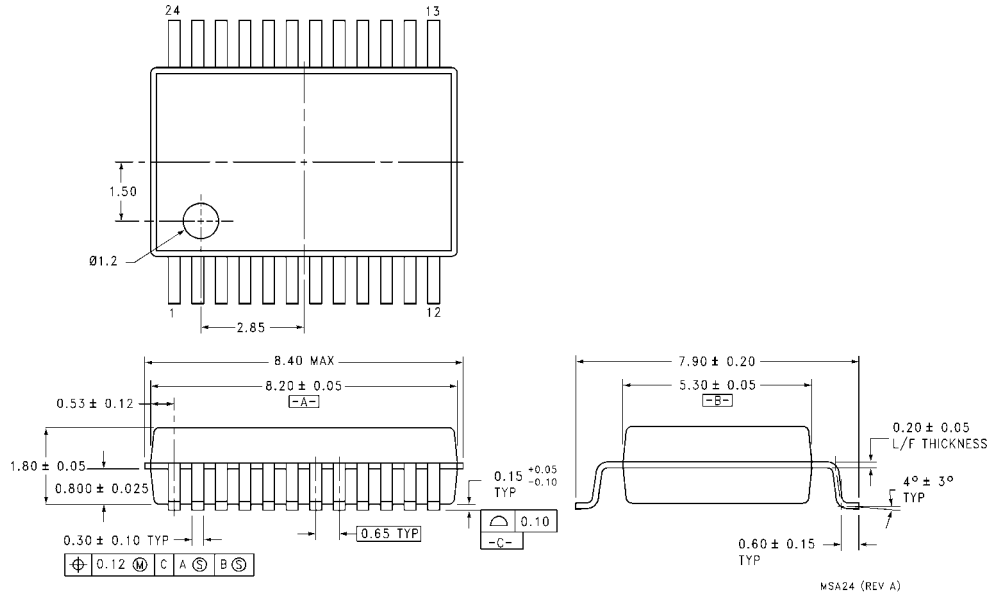


FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted

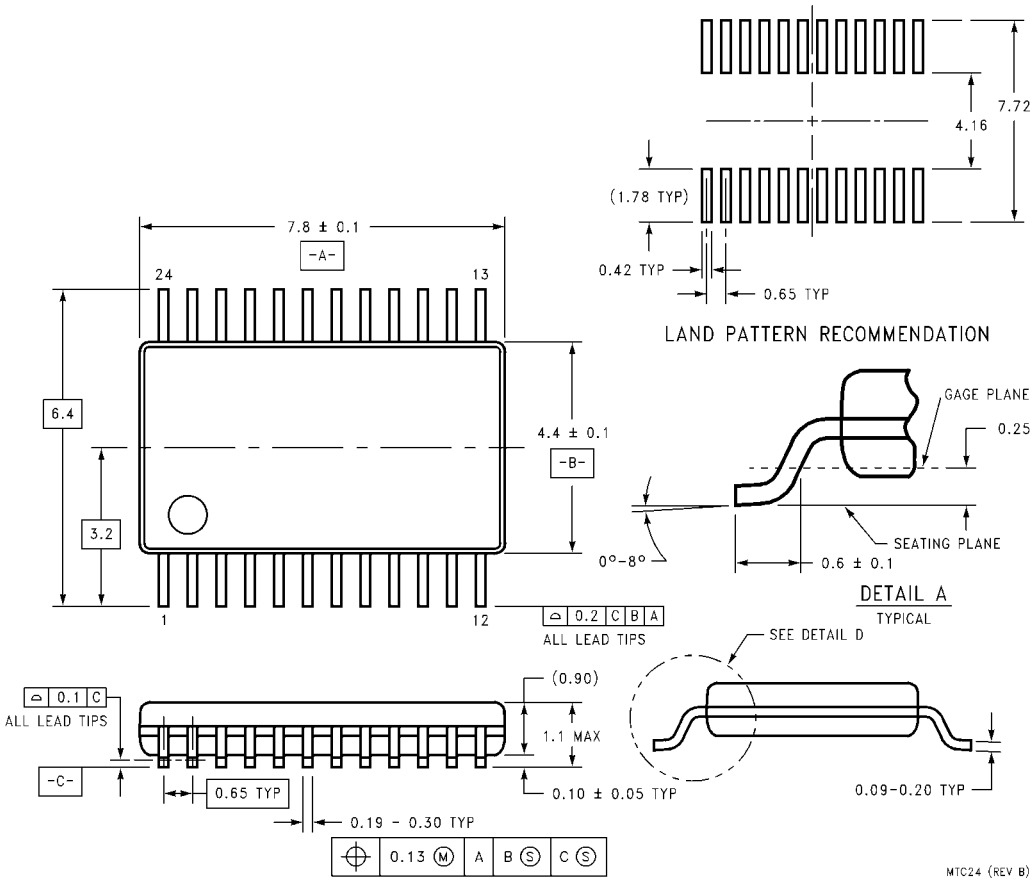


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1993
Revised November 1999

74ABT573
Octal D-Type Latch with 3-STATE Outputs

General Description

The ABT573 is an octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

This device is functionally identical to the ABT373 but has broadside pinouts.

Features

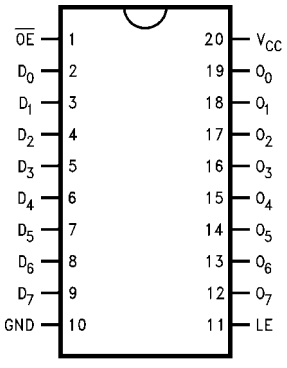
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to ABT373
- 3-STATE outputs for bus interfacing
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch-free bus loading during entire power up and power down
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT573CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT573CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT573CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT573CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ABT573CPC	N20A	20-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-01, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Descriptions
D_0–D_7	Data Inputs
LE	Latch Enable Input (Active HIGH)
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)
O_0–O_7	3-STATE Latch Outputs

Functional Description

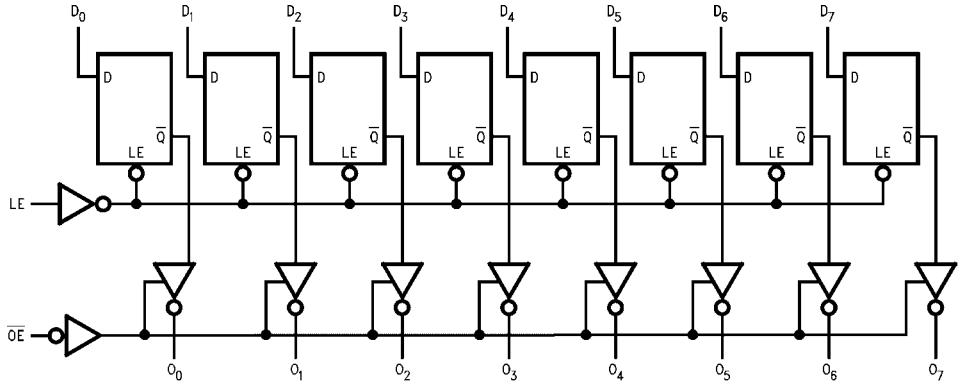
The ABT573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Function Table

Inputs			Outputs
$\overline{OE}$	LE	D	O
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
O_0 = Value stored from previous clock cycle

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	Twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1 1	μA	Max	V_{IN} = 2.7V (Note 4) V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1 −1	μA	Max	V_{IN} = 0.5V (Note 4) V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−10	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 4)	No Load			0.12	mA/MHz	Max	Outputs Open $\overline{OE}$ = GND, LE = V_{CC} (Note 3) One Bit Toggling, 50% Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed but not tested.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	$T_A = 25°C$ (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.5	–1.2		V	5.0	$T_A = 25°C$ (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	$T_A = 25°C$ (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	$T_A = 25°C$ (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.0	0.7	V	5.0	$T_A = 25°C$ (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.9	2.7	4.5	1.9	4.5	ns
t_{PHL}	D_n to O_n	1.9	2.8	4.5	1.9	4.5	
t_{PLH}	Propagation Delay	2.0	3.1	5.0	2.0	5.0	ns
t_{PHL}	LE to O_n	2.0	3.0	5.0	2.0	5.0	
t_{PZH}	Output Enable Time	1.5	3.1	5.3	1.5	5.3	ns
t_{PZL}		1.5	3.1	5.3	1.5	5.3	
t_{PHZ}	Output Disable Time	2.0	3.6	5.4	2.0	5.4	ns
t_{PLZ}	Time	2.0	3.4	5.4	2.0	5.4	

AC Operating Requirements

(SOIC and SSOP Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100				MHz
$t_S(H)$	Set Time, HIGH	1.5			1.5		ns
$t_S(L)$	or LOW D_n to LE	1.5			1.5		
$t_H(H)$	Hold Time, HIGH	1.0			1.0		ns
$t_H(L)$	or LOW D_n to LE	1.0			1.0		
$t_W(H)$	Pulse Width, LE HIGH	3.0			3.0		ns

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 8)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF (Note 9)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 10)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.2	2.0	6.8	2.0	9.0	ns
t_{PHL}	D_n to O_n	1.5	5.2	2.0	6.8	2.0	9.0	
t_{PLH}	Propagation Delay	1.5	5.5	2.0	7.5	2.0	9.5	ns
t_{PHL}	LE to O_n	1.5	5.5	2.0	7.5	2.0	9.5	
t_{PZH}	Output Enable Time	1.5	6.2	2.0	8.0	2.0	10.5	ns
t_{PZL}		1.5	6.2	2.0	8.0	2.0	10.5	
t_{PHZ}	Output Disable Time	1.0	5.5	(Note 11)		(Note 11)		ns
t_{PLZ}		1.0	5.5					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(Note 12)
(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew, HL Transitions	1.0	1.5	ns
t_{OSLH} (Note 14)	Pin to Pin Skew, LH Transitions	1.0	1.5	ns
t_{PS} (Note 15)	Duty Cycle, LH–HL Skew	1.4	3.5	ns
t_{OST} (Note 14)	Pin to Pin Skew, LH/HL Transitions	1.5	3.9	ns
t_{PV} (Note 16)	Device to Device Skew LH/HL Transitions	2.0	4.0	ns

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 13: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Note 16: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

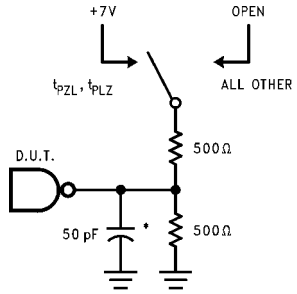
Capacitance

Symbol	Parameter	Typ	Units	Conditions ($T_A = 25°C$)
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$
C_{OUT} (Note 17)	Output Capacitance	9	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency f = 1 MHz per MIL-STD-883B, Method 3012.

Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Tables.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Test Load

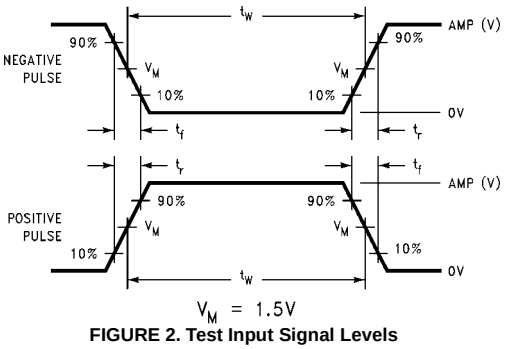


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

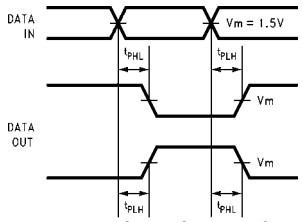


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

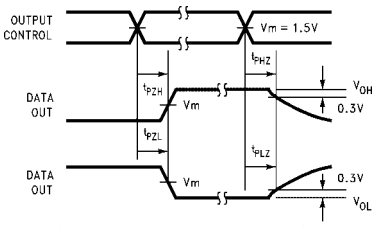


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

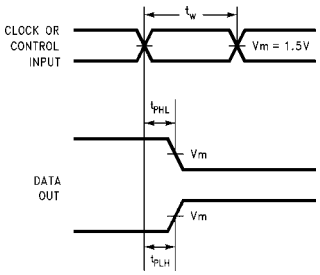


FIGURE 5. Propagation Delay, Pulse Width Waveforms

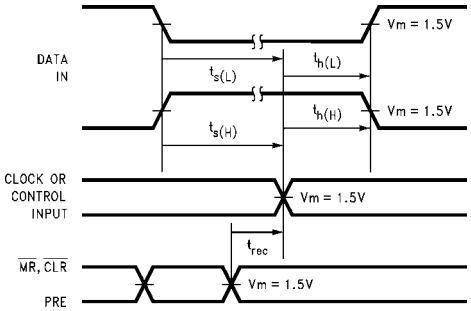
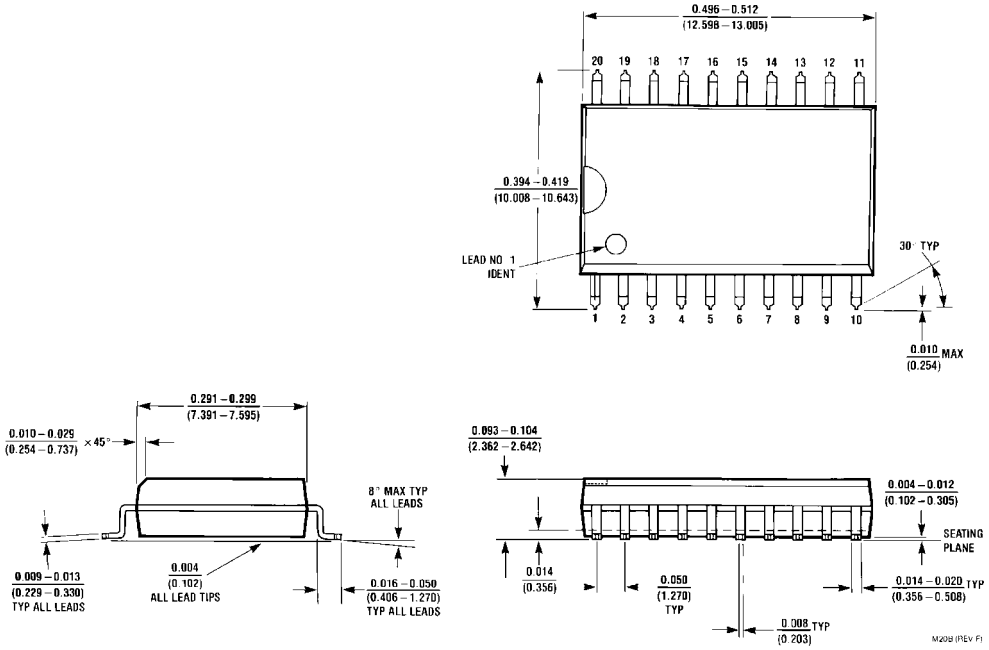


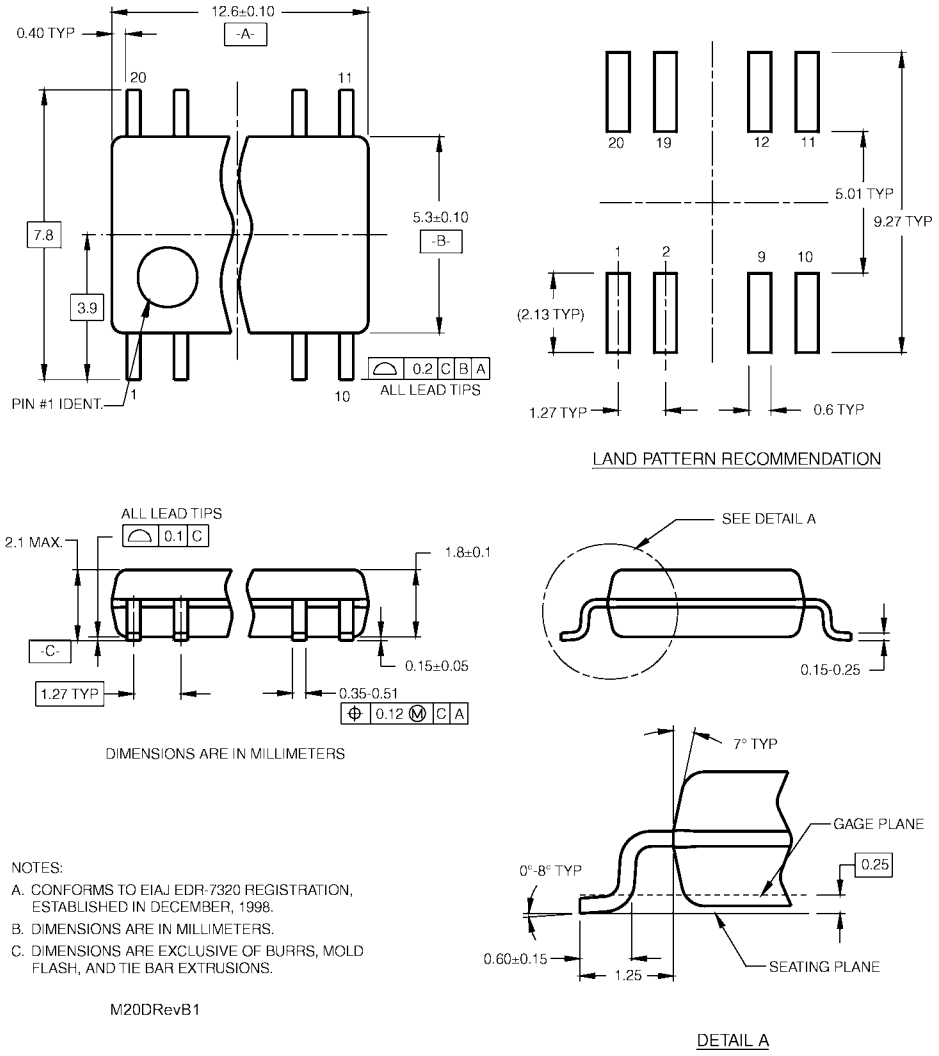
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

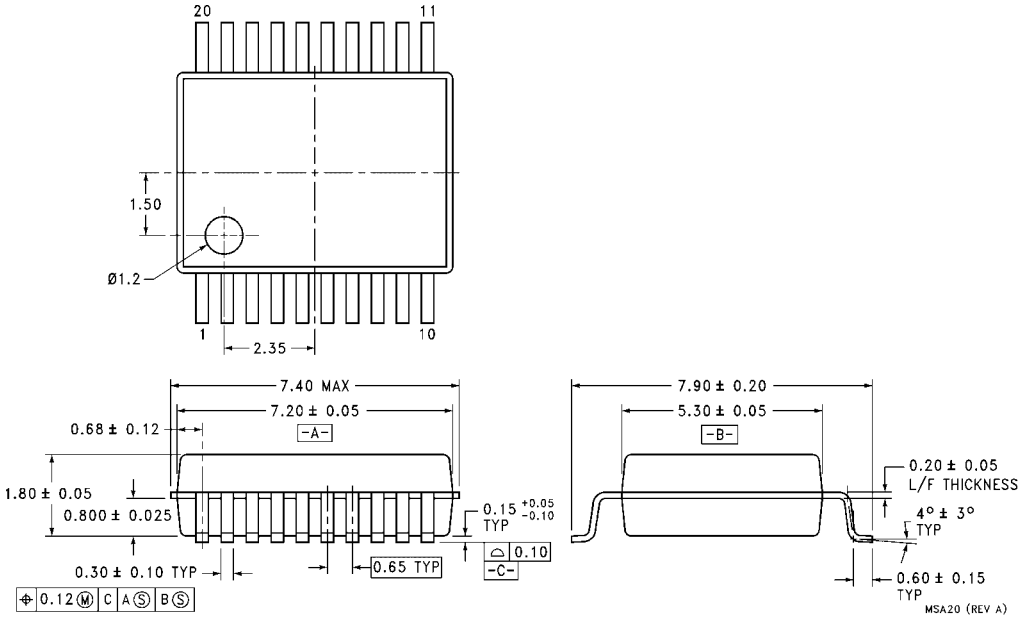
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

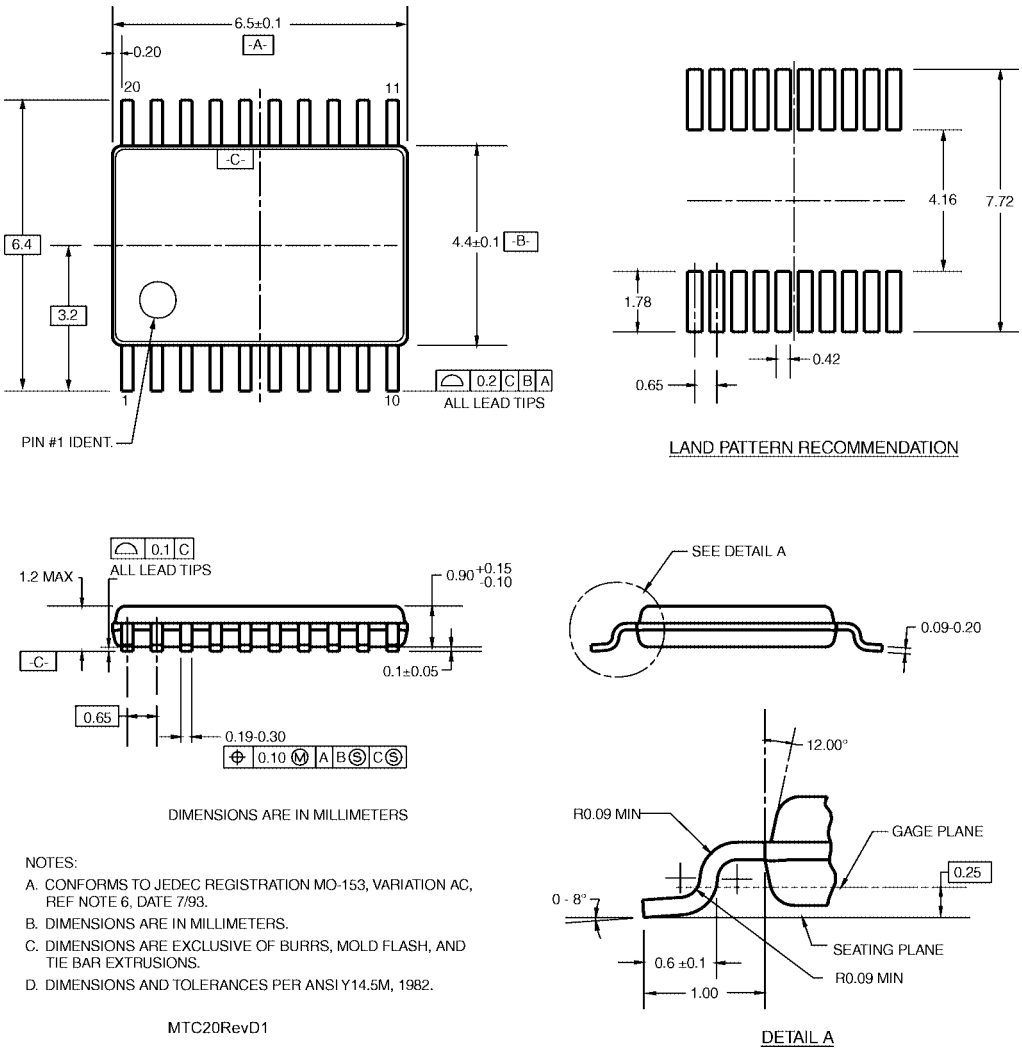
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

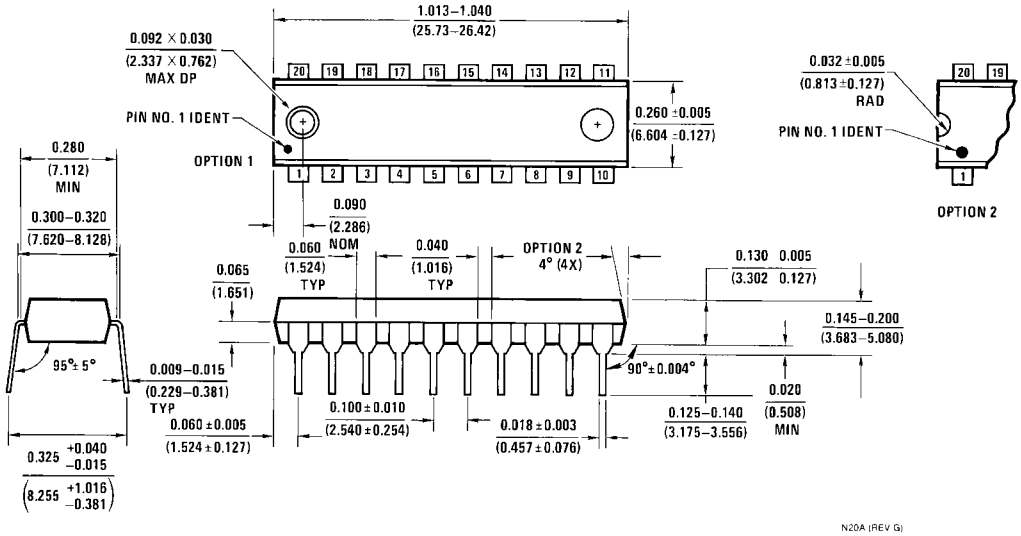
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-01, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1992
Revised November 1999

74ABT574
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The ABT574 is an octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable ($\overline{OE}$). The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The device is functionally identical to the ABT374 but has broadside pinouts.

Features

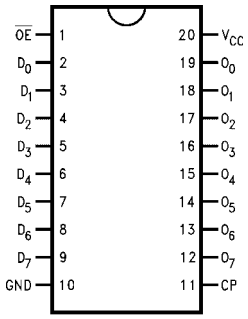
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to ABT374
- 3-STATE outputs for bus-oriented applications
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT574CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT574CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT574CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT574CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input (Active Rising Edge)
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)
O_0–O_7	3-STATE Outputs

Functional Description

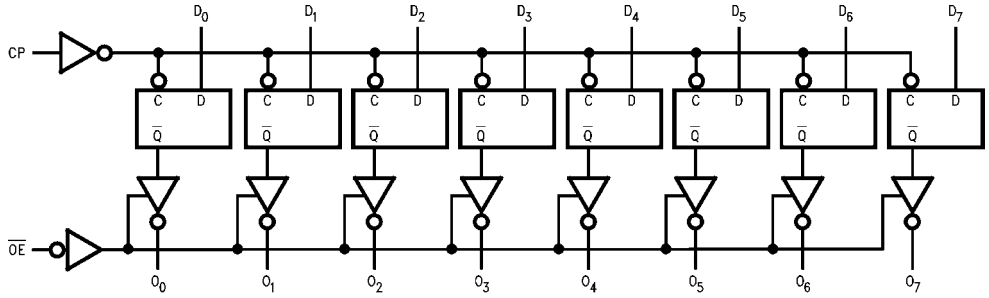
The ABT574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	H or L	L	NC	Z	Hold
H	H or L	H	NC	Z	Hold
H	⌐	L	L	Z	Load
H	⌐	H	H	Z	Load
L	⌐	L	L	L	Data Available
L	⌐	H	H	H	Data Available
L	H or L	L	NC	NC	No Change in Data
L	H or L	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage		2.5			V	Min	I_{OH} = −3 mA
			2.0			V	Min	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage				0.55			I_{OL} = 64 mA
I_{IH}	Input HIGH Current				1	µA	Max	V_{IN} = 2.7V (Note 3)
					1			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−1	µA	Max	V_{IN} = 0.5V (Note 3)
					−1			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OZH}	Output Leakage Current				10	µA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−10	µA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	µA	0.0	V_{OUT} = 5.5V; All Other GND
I_{CCH}	Power Supply Current				50	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	µA	Max	$\overline{OE}$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA		V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA	Max	Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs Open, $\overline{OE}$ = GND,
	(Note 3)				0.30	MHz		One Bit Toggling (Note 4), 50% Duty Cycle

Note 3: Guaranteed, but not tested.

Note 4: For 8-bit toggling, I_{CCD} < 0.8 mA/MHz.

DC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	T_A = 25°C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.5	–1.1		V	5.0	T_A = 25°C (Note 5)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.0	1.6		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T_A = 25°C (Note 7)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = –55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150	200		150		150		MHz
t_{PLH}	Propagation Delay	2.0	3.2	5.0	1.5	7.0	2.0	5.0	ns
t_{PHL}	CP to O_n	2.0	3.3	5.0	1.5	7.4	2.0	5.0	
t_{PZH}	Output Enable Time	1.5	3.1	5.3	1.0	6.5	1.5	5.3	ns
t_{PZL}		1.5	3.1	5.3	1.0	7.2	1.5	5.3	
t_{PHZ}	Output Disable Time	1.5	3.6	5.4	1.0	7.2	1.5	5.4	ns
t_{PLZ}		1.5	3.4	5.4	1.0	6.7	1.5	5.4	

AC Operating Requirements

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = –55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		T_A = –40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	Min	Max	
t_S(H)	Setup Time, HIGH	1.0		1.5		1.0		ns
t_S(L)	or LOW D_n to CP	1.5		2.0		1.5		
t_H(H)	Hold Time, HIGH	1.0		2.0		1.0		ns
t_H(L)	or LOW D_n to CP	1.0		2.0		1.0		
t_W(H)	Pulse Width, CP,	3.0		3.3		3.0		ns
t_W(L)	HIGH or LOW	3.0		3.3		3.0		

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V$ to $5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 8)		$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V$ to $5.5V$ $C_L = 250$ pF (Note 9)		$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V$ to $5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 10)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.7	2.0	7.8	2.0	10.0	ns
t_{PHL}	CP to O_n	1.5	5.7	2.0	7.8	2.0	10.0	
t_{PZH}	Output Enable Time	1.5	6.2	2.0	8.0	2.0	10.5	ns
t_{PZL}		1.5	6.2	2.0	8.0	2.0	10.5	
t_{PHZ}	Output Disable Time	1.0	5.5	(Note 11)		(Note 11)		ns
t_{PLZ}		1.0	5.5					

Note 8: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 9: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 11: The 3-STATE Delay Times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew (Note 12)

(SOIC package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 12)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 13)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew HL Transitions	1.0	1.8	ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Transitions	1.0	1.8	ns
t_{PS} (Note 15)	Duty Cycle LH–HL Skew	1.8	4.3	ns
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Transitions	2.0	4.3	ns
t_{PV} (Note 16)	Device to Device Skew LH/HL Transitions	2.5	4.6	ns

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 13: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

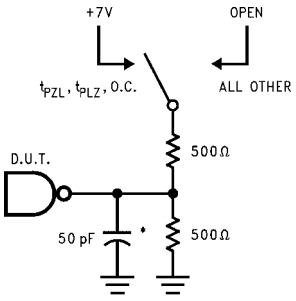
Note 16: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 17)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 17: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

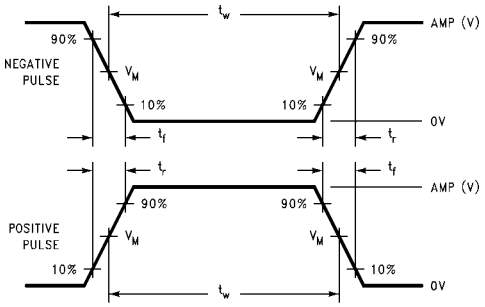


FIGURE 2. V_M = 1.5V

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

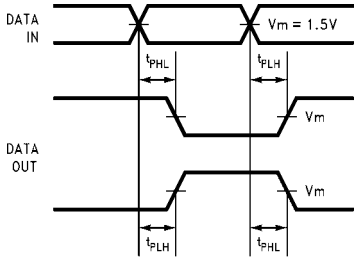


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

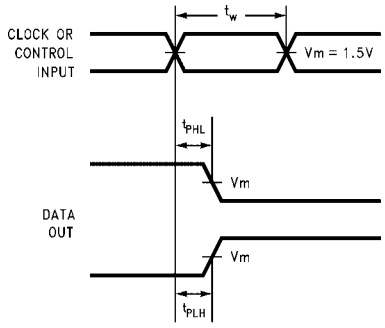


FIGURE 5. Propagation Delay, Pulse Width Waveforms

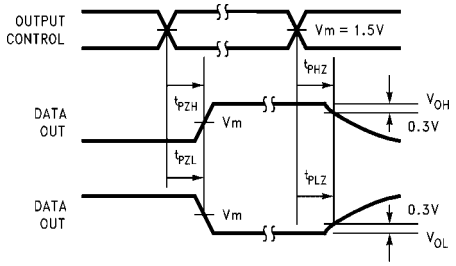


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

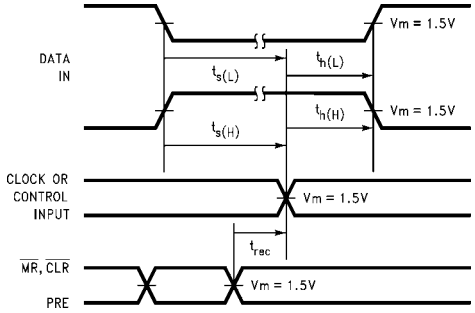
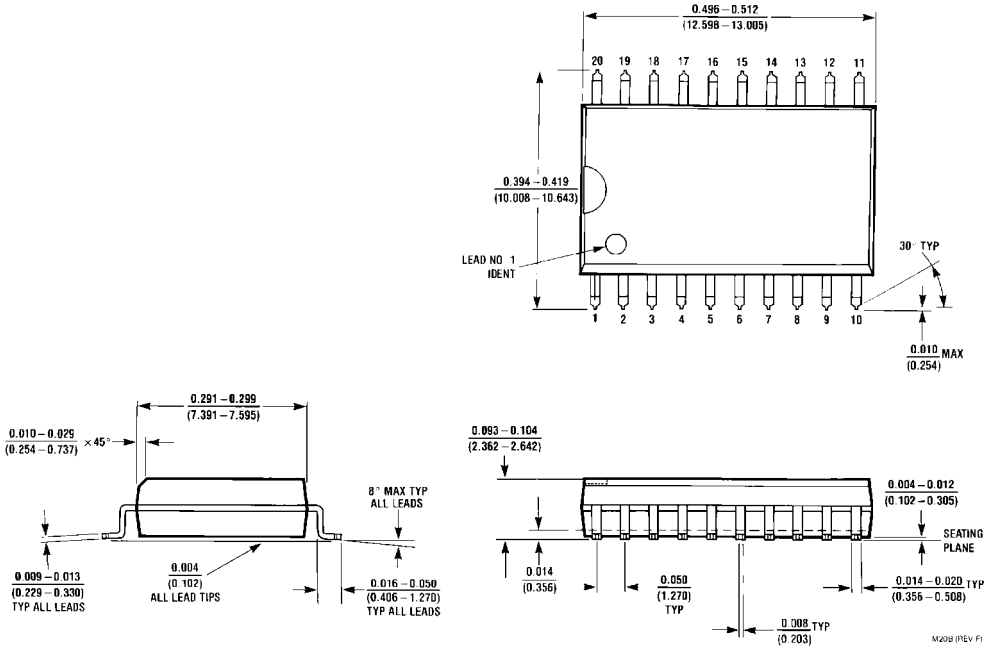


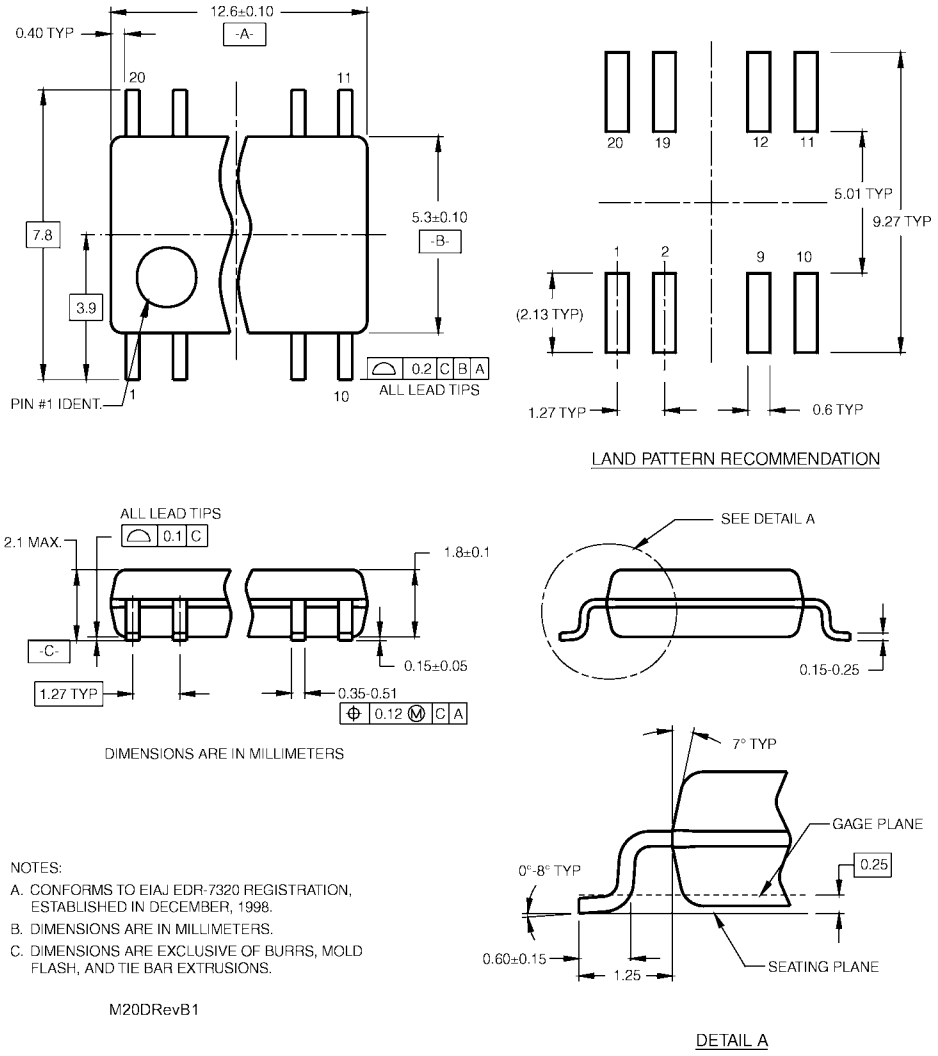
FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

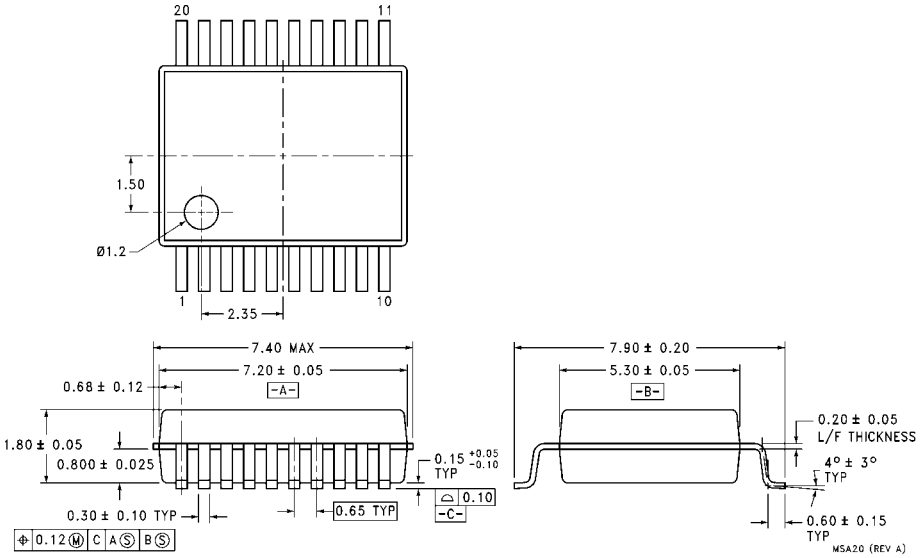
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

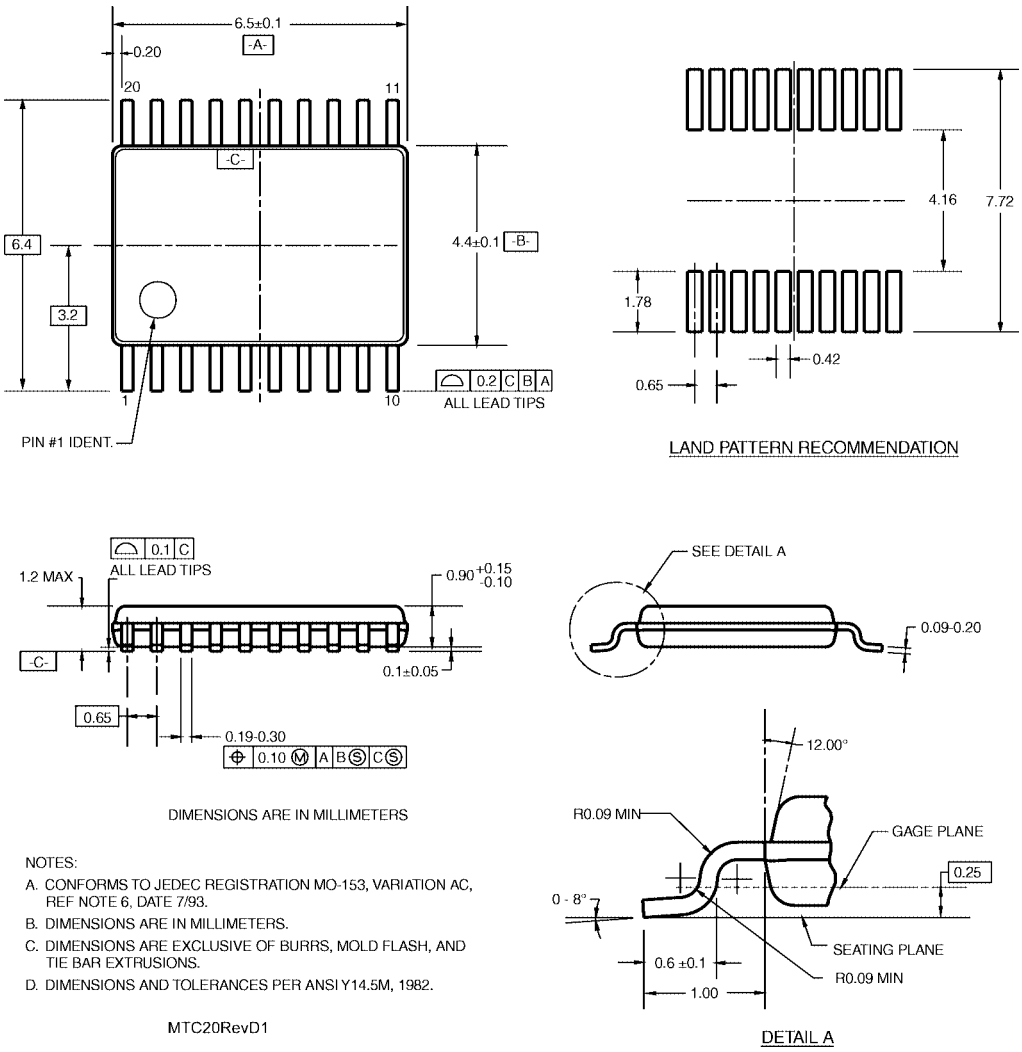
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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April 1992
Revised November 1999

74ABT646
Octal Transceivers and Registers with 3-STATE Outputs

General Description

The ABT646 consists of bus transceiver circuits with 3-STATE, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a high logic level. Control $\overline{OE}$ and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control $\overline{OE}$ is Active LOW. In the isolation mode (control $\overline{OE}$ HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

Features

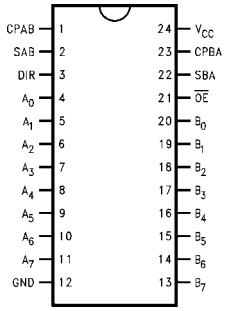
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT646CSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-153, 4.4mm Wide
74ABT646CMSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT646CMTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7	Data Register A Inputs/3-STATE Outputs
B_0–B_7	Data Register B Inputs/3-STATE Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Select Inputs
$\overline{OE}$	Output Enable Input
DIR	Direction Control Input

Truth Table

Inputs						Data I/O (Note 1)		Function
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X	Input	Input	Isolation
H	X	↑	X	X	X			Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X	Input	Output	A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X			Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L	Output	Input	B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L			Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

Real Time Transfer A-Bus to B-Bus

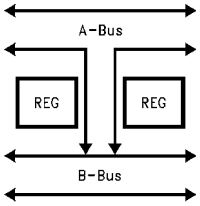


FIGURE 1.

Real Time Transfer B-Bus to A-Bus

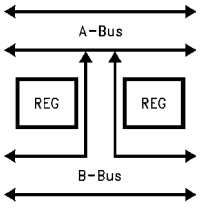


FIGURE 2.

Storage from Bus to Register

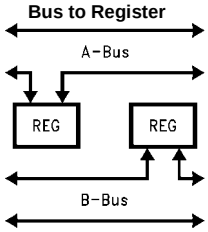


FIGURE 3.

Transfer from Register to Bus

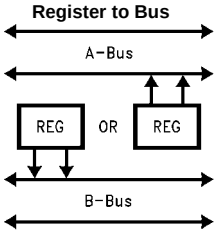
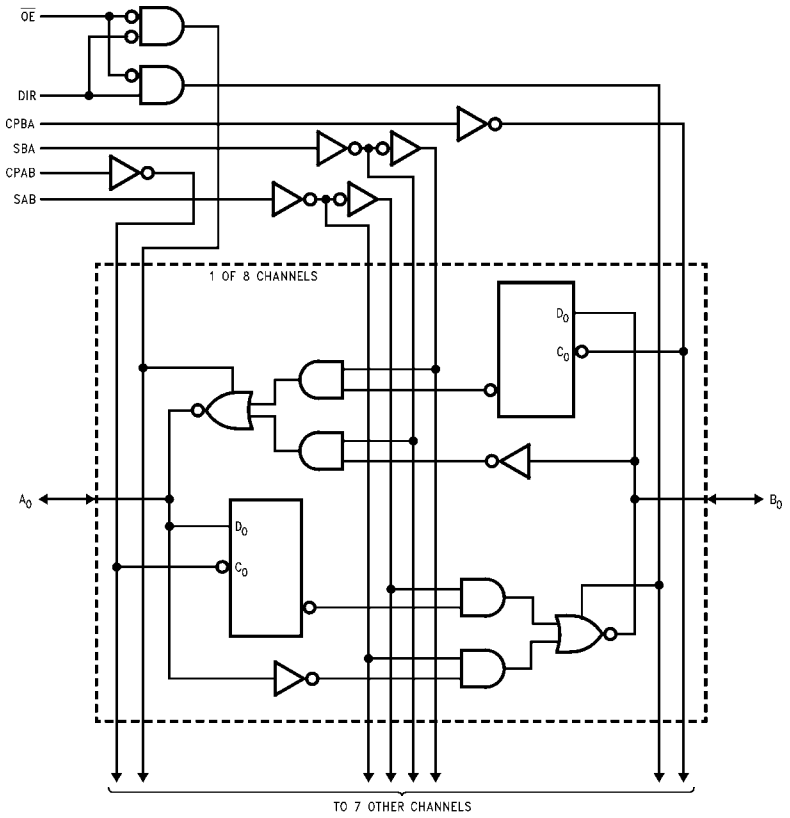


FIGURE 4.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable or	
Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5 2.0					I_{OH} = −3 mA, (A_n, B_n) I_{OH} = −32 mA, (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55			I_{OL} = 64 mA, (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins) All Other Pins Grounded
I_{IH}	Input HIGH Current			1 1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 4) V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1 −1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 4) V_{IN} = 0.0V (Non-I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OE}$ = 2.0V
$I_{IL} + I_{OZL}$	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			250	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			50	µA	Max	Outputs 3-STATE; All Others GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V All Other Outputs at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 4)			0.18	mA/MHz	Max	Outputs OPEN $\overline{OE}$ and DIR = GND, Non-I/O = GND or V_{CC} (Note 5) One Bit toggling, 50% duty cycle

Note 4: Guaranteed but not tested.

Note 5: For 8-bit toggling, I_{CCD} < 1.4 mA/MHz.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.6	0.8	V	5.0	T_A = 25°C (Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	–1.2	–0.9		V	5.0	T_A = 25°C (Note 6)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25° (Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	T_A = 25°C (Note 8)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		0.8	0.5	V	5.0	T_A = 25°C (Note 8)

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 8: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	200			200		200		MHz
t_{PLH}	Propagation Delay	1.7	3.0	5.6	2.2	8.8	1.7	5.6	ns
t_{PHL}	Clock to Bus	1.7	3.4	5.6	1.7	8.8	1.7	5.6	
t_{PLH}	Propagation Delay	1.5	2.6	4.8	1.5	7.9	1.5	4.8	ns
t_{PHL}	Bus to Bus	1.5	3.0	4.8	1.5	7.9	1.5	4.8	
t_{PLH}	Propagation Delay	1.5	3.0	5.9	1.5	8.1	1.5	5.9	ns
t_{PHL}	SBA or SAB to A_n to B_n	1.5	3.4	5.9	1.5	8.9	1.5	5.9	
t_{PZH}	Enable Time	1.5	3.2	6.3	1.0	7.3	1.5	6.3	ns
t_{PZL}	$\overline{OE}$ to $A_n$or B_n	1.5	3.5	6.3	1.9	8.8	1.5	6.3	
t_{PHZ}	Disable Time	1.5	3.7	6.0	1.5	9.3	1.5	6.0	ns
t_{PLZ}	$\overline{OE}$ to $A_n$or B_n	1.5	3.2	6.0	1.5	9.3	1.5	6.0	
t_{PZH}	Enable Time	1.5	3.4	6.3	1.0	7.7	1.5	6.3	ns
t_{PZL}	DIR to A_n or B $_n$	1.5	3.7	6.3	2.2	9.5	1.5	6.3	
t_{PHZ}	Disable Time	1.5	3.8	6.0	1.5	8.7	1.5	6.0	ns
t_{PLZ}	DIR to A_n or B $_n$	1.5	3.2	6.0	1.5	9.2	1.5	6.0	

AC Operating Requirements

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = −55°C to +125°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Max	Min	Max	Min	Max	
t_S(H)	Setup Time, HIGH	1.5		1.5	3.0	1.5		ns
t_S(L)	or LOW Bus to Clock							
t_H(H)	Hold Time, HIGH	1.0		1.0	1.0	1.0		ns
t_H(L)	or LOW Bus to Clock							
t_W(H)	Pulse Width,	3.0		3.0	4.0	3.0		ns
t_W(L)	HIGH or LOW							

Extended AC Electrical Characteristics

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 9)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 10)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 11)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.5	2.0	7.5	2.5	10.0	ns
t_{PHL}	Clock to Bus	1.5	5.5	2.0	7.5	2.5	10.0	
t_{PLH}	Propagation Delay	1.5	6.0	2.0	7.0	2.5	9.5	ns
t_{PHL}	Bus to Bus	1.5	6.0	2.0	7.0	2.5	9.5	
t_{PLH}	Propagation Delay	1.5	6.0	2.0	7.5	2.5	10.0	ns
t_{PHL}	SBA or SAB to A_n or B_n	1.5	6.0	2.0	7.5	2.5	10.0	
t_{PZH}	Output Enable Time	1.5	6.0	2.0	8.0	2.5	10.5	ns
t_{PZL}	$\overline{OE}_n$ or DIR to A_n or B_n	1.5	6.0	2.0	8.0	2.5	10.5	
t_{PHZ}	Output Disable Time	1.5	6.0	(Note 12)		(Note 12)		ns
t_{PLZ}	$\overline{OE}_n$ or DIR to A_n or B_n	1.5	6.0					

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 12: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 13)	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 14)	Units
		Max	Max	
t_{OSHL} (Note 15)	Pin to Pin Skew, HL Transitions	1.3	2.5	ns
t_{OSLH} (Note 15)	Pin to Pin Skew, LH Transitions	1.0	2.0	ns
t_{PS} (Note 16)	Duty Cycle, LH–HL Skew	2.0	4.0	ns
t_{OST} (Note 15)	Pin to Pin Skew, LH/HL Transitions	2.0	4.0	ns
t_{PV} (Note 17)	Device to Device Skew, LH/HL Transitions	2.5	4.5	ns

Note 13: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 14: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 16: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

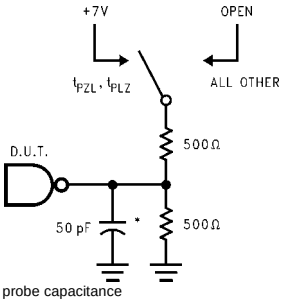
Note 17: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$ (non I/O pins)
$C_{I/O}$ (Note 18)	Output Capacitance	11	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 18: $C_{I/O}$ is measured at frequency, f = 1 MHz, per MIL-STD-883, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 5. Standard AC Test Load

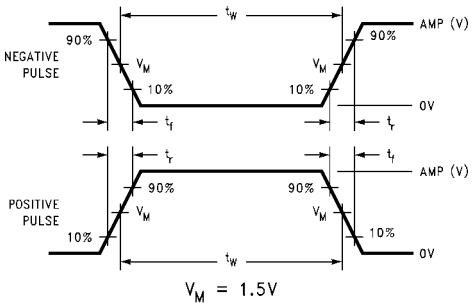


FIGURE 6. Test Input Signal Levels Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 7. Test Input Signal Requirements

AC Waveforms

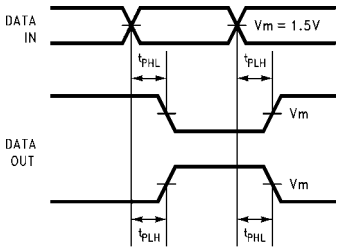


FIGURE 8. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

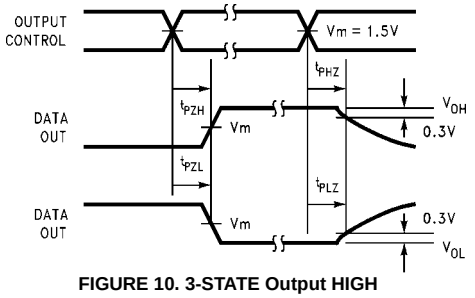


FIGURE 10. 3-STATE Output HIGH and LOW Enable and Disable Times

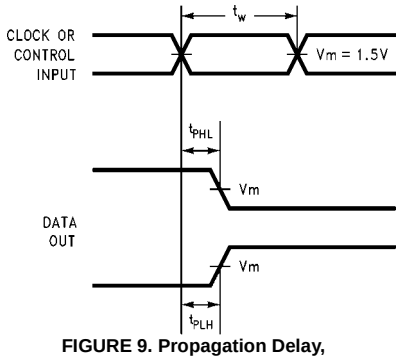


FIGURE 9. Propagation Delay, Pulse Width Waveforms

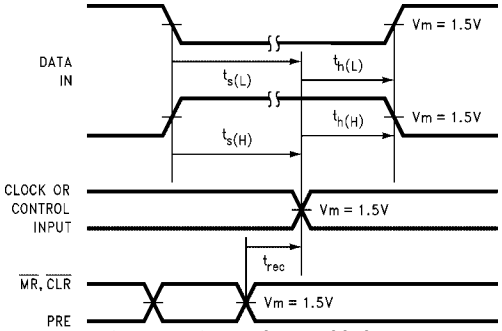
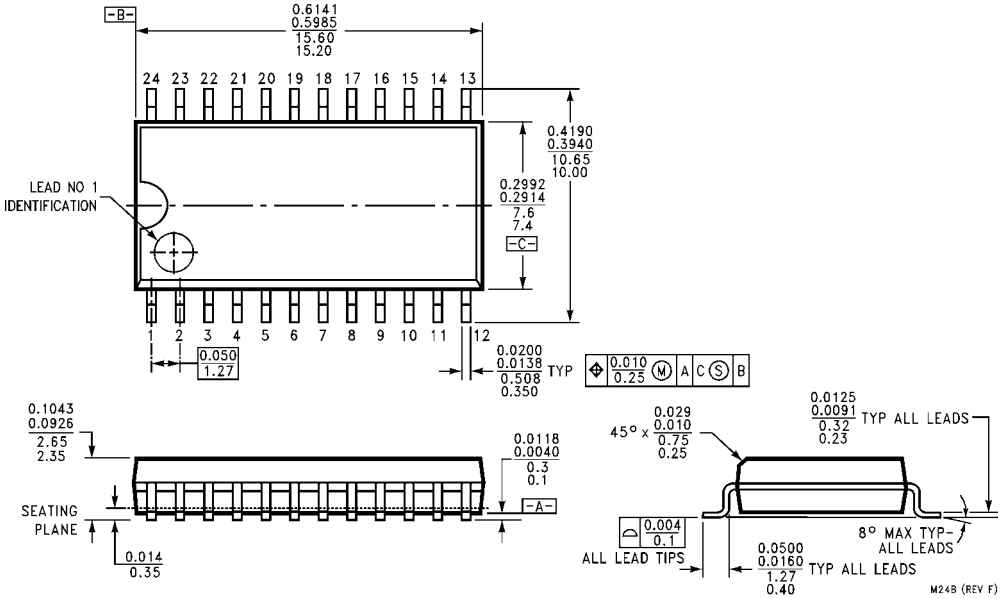
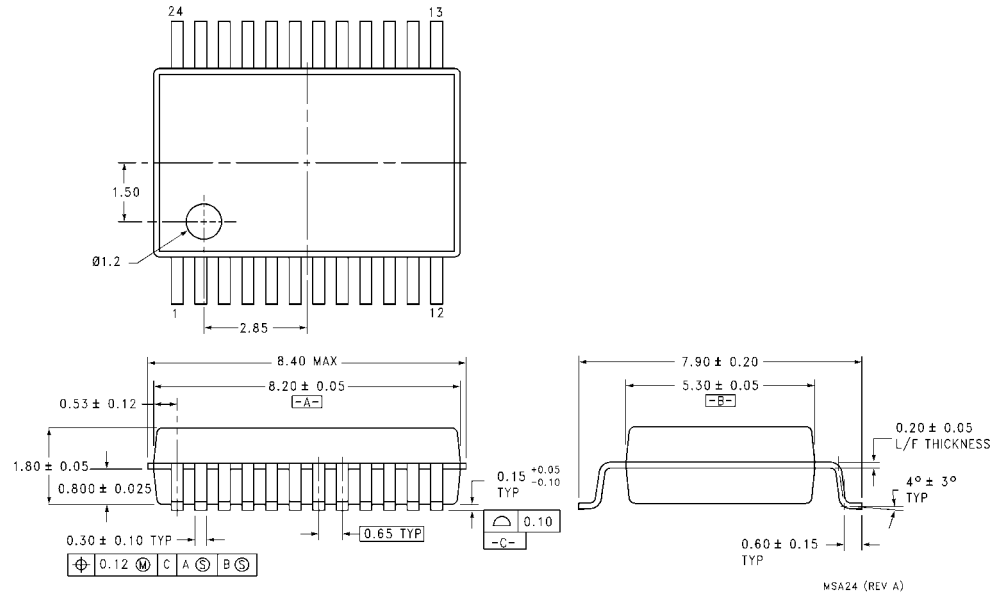


FIGURE 11. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted

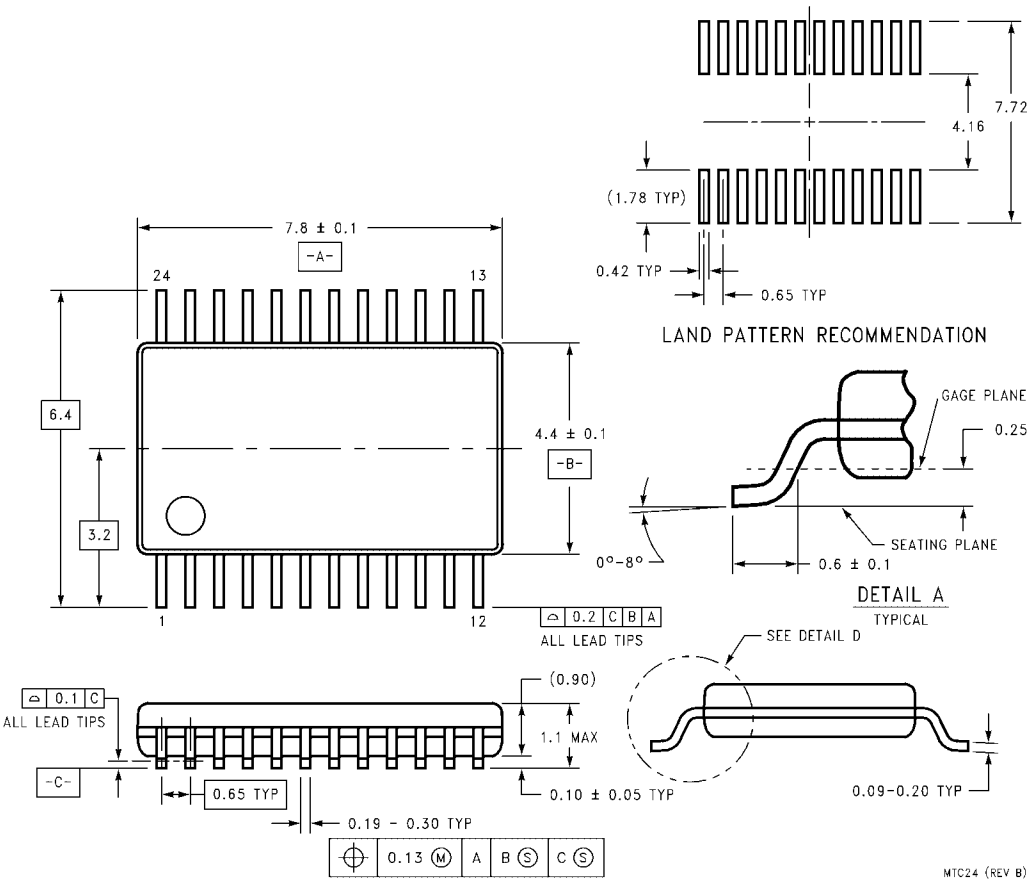


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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November 1992
Revised January 1999

74ABT652
Octal Transceivers and Registers with 3-STATE Outputs

General Description

The ABT652 consists of bus transceiver circuits with D-type flip-flops and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, $\overline{\text{OEBA}}$) are provided to control the transceiver function.

Features

- Independent registers for A and B buses
- Multiplexed real-time and stored data
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

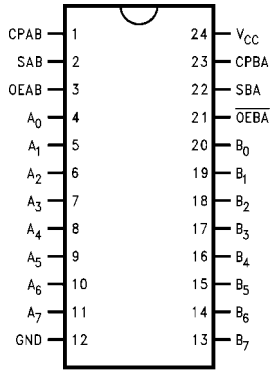
Ordering Code:

Order Number	Package Number	Package Description
74ABT652CSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT652CMSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT652CMTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for SOIC, SSOP and TSSOP



Pin Descriptions

Pin Names	Description
A_0–A_7	Data Register A Inputs/3-STATE Outputs
B_0–B_7	Data Register B Inputs/3-STATE Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{\text{OEBA}}$	Output Enable Inputs

Truth Table

Inputs						Inputs/Outputs (Note 1)		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW to HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW to HIGH transition on the clock inputs.

Functional Description

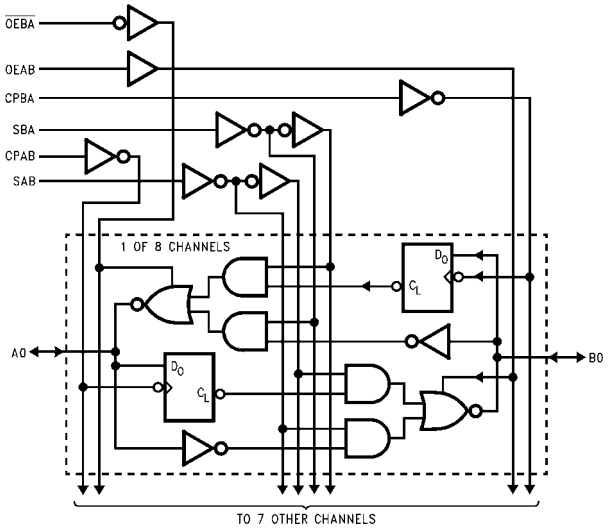
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in Figure 1 demonstrate the four fundamental bus-management functions that can be performed with the ABT652.

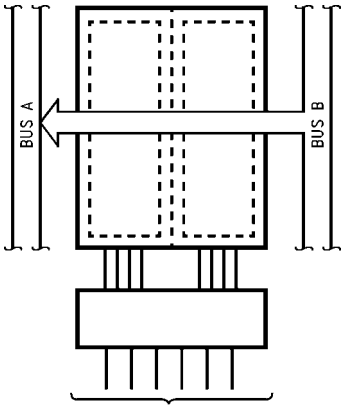
Data on the A or B data bus, or both, can be stored in the internal D flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB and $\overline{OEBA}$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Logic Diagram



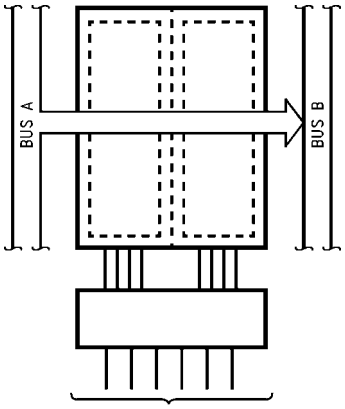
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Note A: Real-Time Transfer Bus B to Bus A



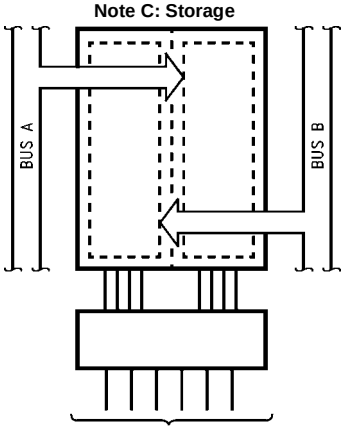
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Note B: Real-Time Transfer Bus A to Bus B



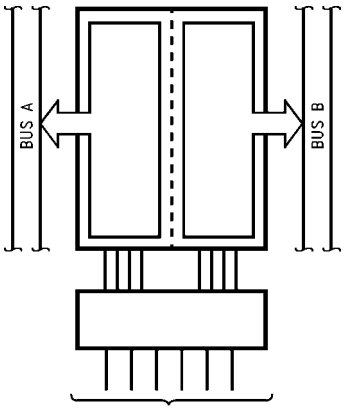
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

Note C: Storage



OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
X	H	⌐	X	X	X
L	X	X	⌐	X	X
L	H	⌐	⌐	X	X

Note D: Transfer Storage Data to A or B



OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

FIGURE 1.

Absolute Maximum Ratings (Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable	
or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate (ΔV/Δt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH	2.5			V	Min	I_{OH} = −3 mA, (A_n, B_n)
	Voltage	2.0					I_{OH} = −32 mA, (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA, (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins)
							All Other Pins Grounded
I_{IH}	Input HIGH Current			1	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 4)
				1			V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−1	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 4)
				−1			V_{IN} = 0.0V (Non-I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			10	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{OEBA}$ = 2.0V and OEAB = GND = 2.0V
I_{IL} + I_{OZL}	Output Leakage Current			−10	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{OEBA}$ = 2.0V and OEAB = GND = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n); All Others GND
I_{CCH}	Power Supply Current			250	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			50	µA	Max	Outputs 3-STATE; All others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V; All others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} No Load (Note 6)			0.18	mA/MHz	Max	Outputs Open (Note 5); OEAB = $\overline{OEBA}$ = GND; One bit toggling, 50% duty cycle

Note 4: Guaranteed but not tested.

Note 5: For 8 outputs toggling, I_{CCD} < 1.4 mA/MHz.

Note 6: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.6	0.8	V	5.0	T_A = 25°C (Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.2	−0.9		V	5.0	T_A = 25°C (Note 7)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 8)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	T_A = 25°C (Note 9)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		0.8	0.4	V	5.0	T_A = 25°C (Note 9)

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 8: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 9: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f_{max}	Max Clock Frequency	200			200		MHz
t_{PLH}	Propagation Delay	1.7	3.0	4.9	1.7	4.9	ns
t_{PHL}	Clock to Bus	1.7	3.4	4.9	1.7	4.9	
t_{PLH}	Propagation Delay	1.5	2.6	4.5	1.5	4.5	ns
t_{PHL}	Bus to Bus	1.5	3.0	4.5	1.5	4.5	
t_{PLH}	Propagation Delay	1.5	3.0	5.0	1.5	5.0	ns
t_{PHL}	SBA or SAB to A_n to B_n	1.5	3.4	5.0	1.5	5.0	
t_{PZH}	Enable Time	1.5	3.3	5.5	1.5	5.5	ns
t_{PZL}	$\overline{OEBA}$ or OEAB to A_n or B_n	1.5	3.7	5.5	1.5	5.5	
t_{PHZ}	Disable Time	1.5	3.7	6.0	1.5	6.0	ns
t_{PLZ}	$\overline{OEBA}$ or OEAB to A_n or B_n	1.5	3.3	6.0	1.5	6.0	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW Bus to Clock	1.5		1.5		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW Bus to Clock	1.0		1.0		ns
$t_W(H)$ $t_W(L)$	Pulse Width, HIGH or LOW	3.0		3.0		ns

Extended AC Electrical Characteristics

(SOIC package):

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 10)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 11)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 12)		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay Clock to Bus	1.5 1.5	5.5 5.5	2.0 2.0	7.5 7.5	2.5 2.5	10.0 10.0	ns
t_{PLH} t_{PHL}	Propagation Delay Bus to Bus	1.5 1.5	6.0 6.0	2.0 2.0	7.0 7.0	2.5 2.5	9.5 9.5	ns
t_{PLH} t_{PHL}	Propagation Delay SBA or SAB to A_n or B_n	1.5 1.5	6.0 6.0	2.0 2.0	7.5 7.5	2.5 2.5	10.0 10.0	 ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OEBA}$ or OEAB to A_n or B_n	1.5 1.5	6.0 6.0	2.0 2.0	8.0 8.0	2.5 2.5	11.5 11.5	 ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OEBA}$ or OEAB to A_n or B_n	1.5 1.5	6.0 6.0	(Note 13)		(Note 13)		 ns

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: The 3-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 8 Outputs Switching (Note 16)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 8 Outputs Switching (Note 17)	Units
		Max	Max	
t_{OSHL} (Note 14)	Pin to Pin Skew HL Transitions	1.3	2.5	ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Transitions	1.0	2.0	ns
t_{PS} (Note 18)	Duty Cycle LH–HL Skew	2.0	4.0	ns
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Transitions	2.0	4.0	ns
t_{PV} (Note 15)	Device to Device Skew LH/HL Transitions	2.5	4.5	ns

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}). This specification is guaranteed but not tested.

Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested

Note 16: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 17: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

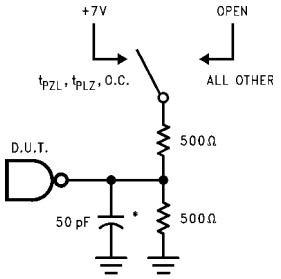
Note 18: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions ($T_A = 25°C$)
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$ (non I/O pins)
$C_{I/O}$ (Note 19)	I/O Capacitance	11.0	pF	$V_{CC} = 5.0V$ (A_n, B_n)

Note 19: $C_{I/O}$ is measured at frequency, f = 1 MHz, per MIL-STD-883D, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 2. Standard AC Test Load

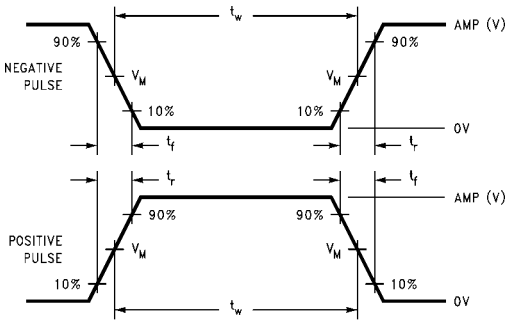


FIGURE 3. Test Input Signal Levels

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 4. Test Input Signal Requirements

AC Waveforms

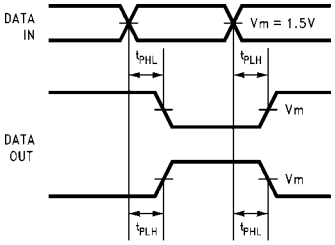


FIGURE 5. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

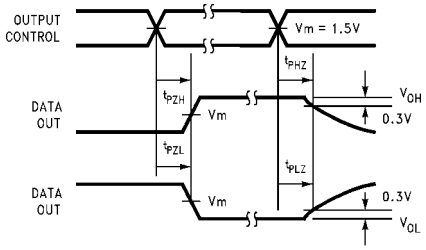


FIGURE 7. 3-STATE Output HIGH and LOW Enable and Disable Times

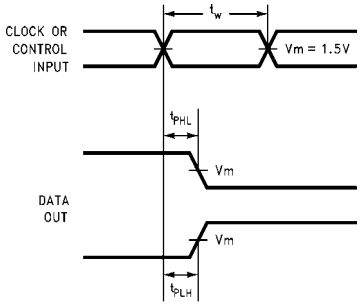


FIGURE 6. Propagation Delay, Pulse Width Waveforms

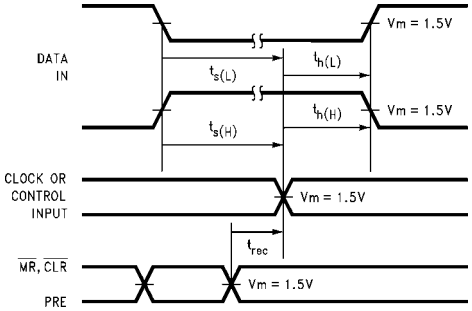
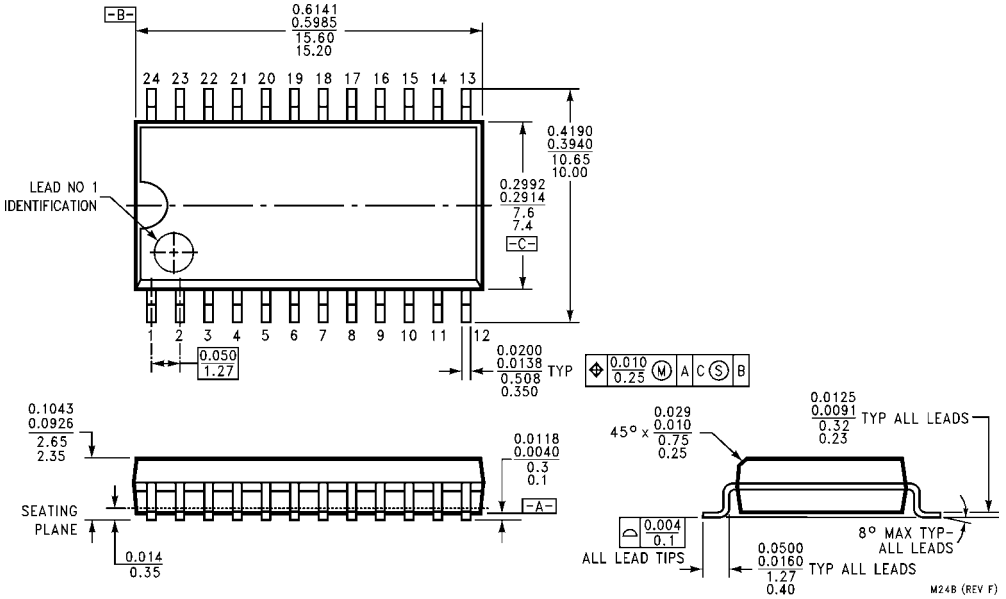
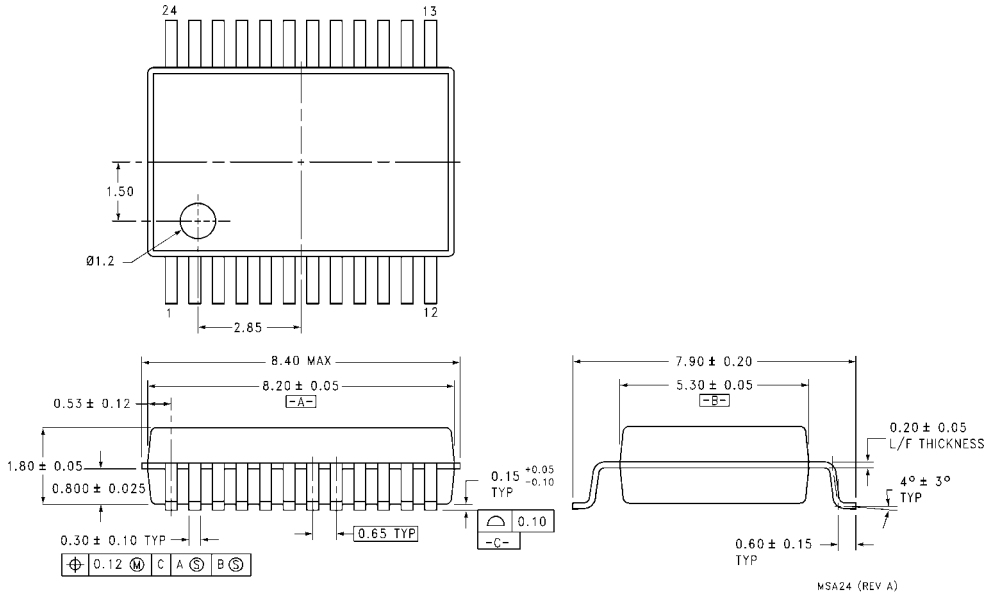


FIGURE 8. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted

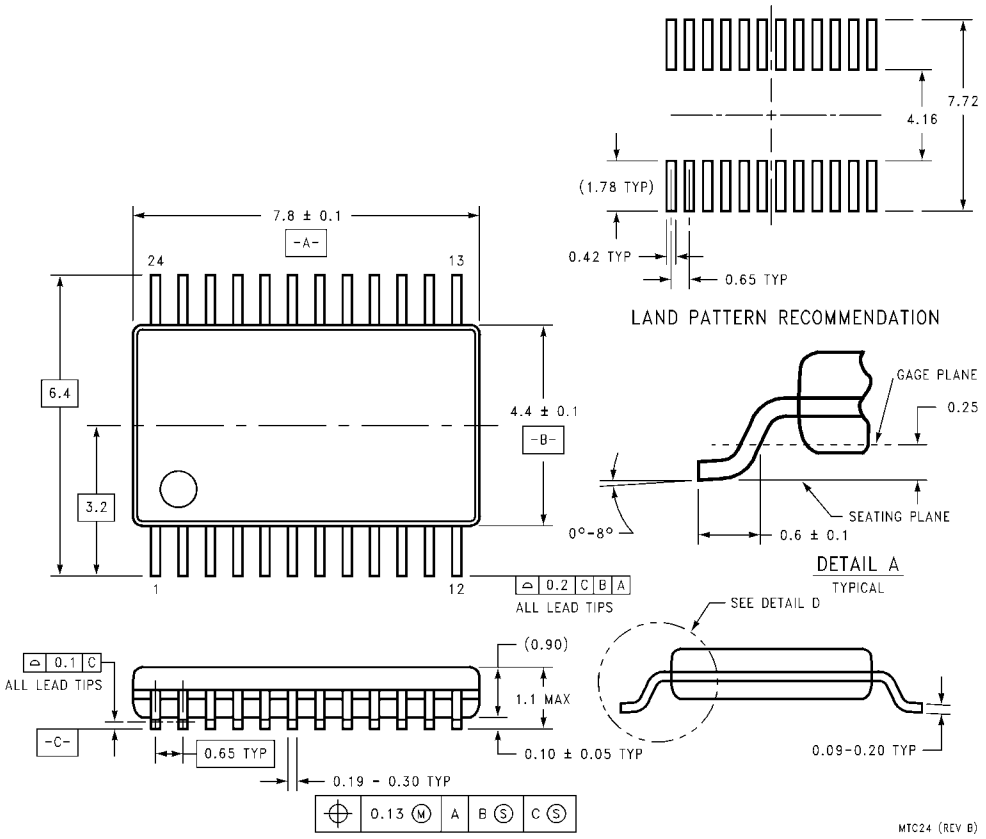


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised January 1999

74ABT899
9-Bit Latchable Transceiver with Parity Generator/Checker

General Description

The ABT899 is a 9-bit to 9-bit parity transceiver with transparent latches. The device can operate as a feed-through transceiver or it can generate/check parity from the 8-bit data busses in either direction.

The ABT899 features independent latch enables for the A-to-B direction and the B-to-A direction, a select pin for ODD/$\overline{\text{EVEN}}$ parity, and separate error signal output pins for checking parity.

Features

- Latchable transceiver with output sink of 64 mA
- Option to select generate parity and check or "feed-through" data/parity in directions A-to-B or B-to-A
- Independent latch enables for A-to-B and B-to-A directions
- Select pin for ODD/$\overline{\text{EVEN}}$ parity
- $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ output pins for parity checking
- Ability to simultaneously generate and check parity
- May be used in systems applications in place of the 543 and 280
- May be used in system applications in place of the 657 and 373 (no need to change T/$\overline{\text{R}}$ to check parity)
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

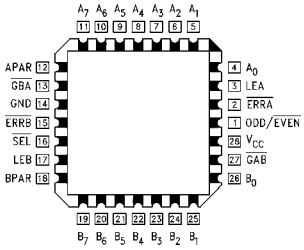
Ordering Code:

Order Number	Package Number	Package Description
74ABT899CSC	M28B	28-Lead Small Outline Integrated Circuit (SOIC), MS-013, 0.300" Wide Body
74ABT899CMSA	MSA28	28-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT899CQC	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450" Square

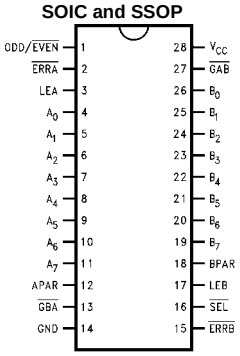
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagrams

Pin Assignment for PLCC



Pin Assignment for SOIC and SSOP



Pin Descriptions

Pin Names	Descriptions
A_0–A_7	A Bus Data Inputs/Data Outputs
B_0–B_7	B Bus Data Inputs/Data Outputs
APAR, BPAR	A and B Bus Parity Inputs/Outputs
ODD/$\overline{\text{EVEN}}$	ODD/$\overline{\text{EVEN}}$ Parity Select, Active LOW for EVEN Parity
$\overline{\text{GBA}}$, $\overline{\text{GAB}}$	Output Enables for A or B Bus, Active LOW
$\overline{\text{SEL}}$	Select Pin for Feed-Through or Generate Mode, LOW for Generate Mode
LEA, LEB	Latch Enables for A and B Latches, HIGH for Transparent Mode
$\overline{\text{ERRA}}$, $\overline{\text{ERRB}}$	Error Signals for Checking Generated Parity with Parity In, LOW if Error Occurs

Functional Description

The ABT899 has three principal modes of operation which are outlined below. These modes apply to both the A-to-B and B-to-A directions.

- Bus A (B) communicates to Bus B (A), parity is generated and passed on to the B (A) Bus as BPAR (APAR). If LEB (LEA) is HIGH and the Mode Select ($\overline{\text{SEL}}$) is LOW, the parity generated from B[0:7] (A[0:7]) can be checked and monitored by $\overline{\text{ERRB}}$ ($\overline{\text{ERRA}}$).
- Bus A (B) communicates to Bus B (A) in a feed-through mode if $\overline{\text{SEL}}$ is HIGH. Parity is still generated and checked as $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ in the feed-through mode (can be used as an interrupt to signal a data/parity bit error to the CPU).
- Independent Latch Enables (LEA and LEB) allow other permutations of generating/checking (see Function Table below).

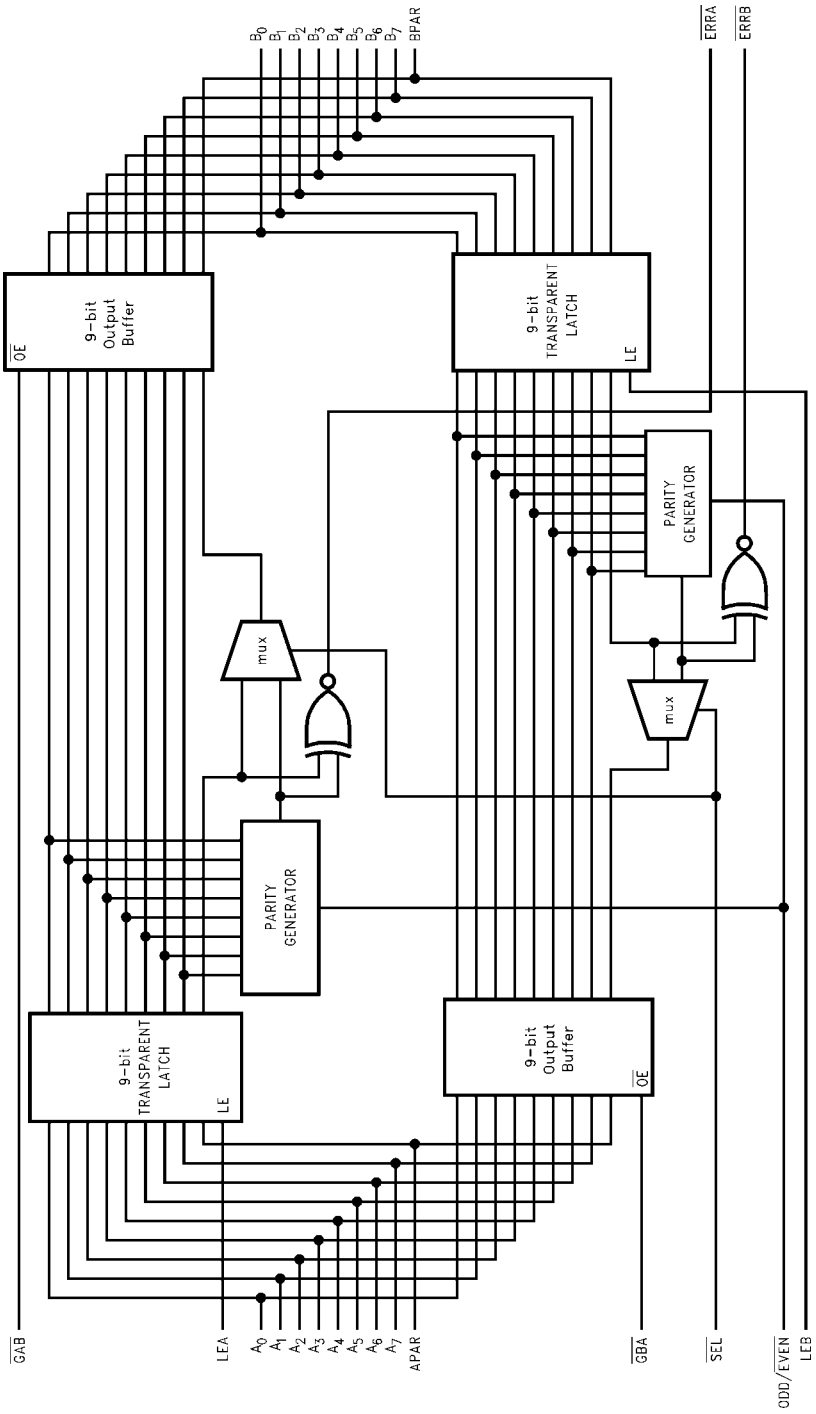
Function Table

Inputs					Operation
$\overline{\text{GAB}}$	$\overline{\text{GBA}}$	$\overline{\text{SEL}}$	LEA	LEB	
H	H	X	X	X	Busses A and B are 3-STATE.
H	L	L	L	H	Generates parity from B[0:7] based on O/$\overline{\text{E}}$ (Note 1). Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$.
H	L	L	H	H	Generates parity from B[0:7] based on O/$\overline{\text{E}}$. Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$. Generated parity also fed back through the A latch for generate/check as $\overline{\text{ERRA}}$.
H	L	L	X	L	Generates parity from B latch data based on O/$\overline{\text{E}}$. Generated parity → APAR. Generated parity checked against latched BPAR and output as $\overline{\text{ERRB}}$.
H	L	H	X	H	BPAR/B[0:7] → APAR/A0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$.
H	L	H	H	H	BPAR/B[0:7] → APAR/A[0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$. Generated parity also fed back through the A latch for generate/check as $\overline{\text{ERRA}}$.
L	H	L	H	L	Generates parity for A[0:7] based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$.
L	H	L	H	H	Generates parity from A[0:7] based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$. Generated parity also fed back through the B latch for generate/check as $\overline{\text{ERRB}}$.
L	H	L	L	X	Generates parity from A latch data based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against latched APAR and output as $\overline{\text{ERRA}}$.
L	H	H	H	L	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$.
L	H	H	H	H	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$. Generated parity also fed back through the B latch for generate/check as $\overline{\text{ERRB}}$.

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Note 1: O/$\overline{\text{E}}$ = ODD/$\overline{\text{EVEN}}$

Functional Block Diagram



Absolute Maximum Ratings (Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	−40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	2.5 2.0			V	Min	I_{OH} = −3 mA, (A_n, B_n, APAR, BPAR) I_{OH} = −32 mA, (A_n, B_n, APAR, BPAR)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA, (A_n, B_n, APAR, BPAR)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, (Non-I/O Pins) All Other Pins Grounded
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V (Non-I/O Pins) (Note 4) V_{IN} = V_{CC} (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n, APAR, BPAR)
I_{IL}	Input LOW Current			−5	µA	Max	V_{IN} = 0.5V (Non-I/O Pins) (Note 4) V_{IN} = 0.0V (Non-I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			50	µA	0V–5.5V	V_{OUT} = 2.7V (A_n, B_n); $\overline{GAB}$ and $\overline{GBA}$ = 2.0V
$I_{IL} + I_{OZL}$	Output Leakage Current			−50	µA	0V–5.5V	V_{OUT} = 0.5V (A_n, B_n); $\overline{GAB}$ and $\overline{GBA}$ = 2.0V
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0V (A_n, B_n, APAR, BPAR)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n, APAR, BPAR)
I_{ZZ}	Bus Drainage Test			100	µA	0.0V	V_{OUT} = 5.5V (A_n, B_n, APAR, BPAR); All Others GND
I_{CCH}	Power Supply Current			250	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			34	mA	Max	All Outputs LOW, ERRA/B = HIGH (Note 5)
I_{CCZ}	Power Supply Current			250	µA	Max	Outputs 3-STATE All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input			2.5	mA	Max	V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC}: No Load (Note 4)			0.4	mA/MHz	Max	Outputs Open $\overline{GAB}$ or $\overline{GBA}$ = GND, LE = HIGH Non-I/O = GND or V_{CC} One bit toggling, 50% duty cycle

Note 4: Guaranteed, but not tested.

Note 5: Add 3.75 mA for each $\overline{ERR}$ LOW.

DC Electrical Characteristics

(PLCC package)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.8	1.1	V	5.0	T_A = 25°C (Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.3	−0.8		V	5.0	T_A = 25°C (Note 6)
V_{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 8)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	T_A = 25°C (Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage		0.8	0.5	V	5.0	T_A = 25°C (Note 7)

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 8: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and PLCC Package)

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −40°C to +85°C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	3.0	4.8	1.5	4.8	ns
t_{PHL}	A_n, to B_n	1.5	3.5	4.8	1.5	4.8	
t_{PLH}	Propagation Delay	2.5	5.9	9.2	2.5	9.2	ns
t_{PHL}	A_n, B_n to BPAR, APAR	2.5	5.8	9.2	2.5	9.2	
t_{PLH}	Propagation Delay	2.5	5.4	8.5	2.5	8.5	ns
t_{PHL}	A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$	2.5	5.4	8.5	2.5	8.5	
t_{PLH}	Propagation Delay	1.5	3.7	6.0	1.5	6.0	ns
t_{PHL}	APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$	1.5	3.7	6.0	1.5	6.0	
t_{PLH}	Propagation Delay	2.0	4.4	6.9	2.0	6.9	ns
t_{PHL}	ODD/EVEN to APAR, BPAR	2.0	4.4	6.9	2.0	6.9	
t_{PLH}	Propagation Delay	1.8	4.0	6.0	1.8	6.0	ns
t_{PHL}	ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$	1.8	4.0	6.0	1.8	6.0	
t_{PLH}	Propagation Delay	1.5	3.8	6.0	1.5	6.0	ns
t_{PHL}	SEL to APAR, BPAR	1.5	3.8	6.0	1.5	6.0	
t_{PLH}	Propagation Delay	1.5	3.2	4.6	1.5	4.6	ns
t_{PHL}	LEA, LEB to B_n, A_n	1.5	3.2	4.6	1.5	4.6	
t_{PLH}	Propagation Delay	2.5	5.9	8.8	2.5	8.8	
t_{PHL}	LEA, LEB to BPAR, APAR Generate Mode	2.5	5.7	8.8	2.5	8.8	ns
t_{PLH}	Propagation Delay	1.5	3.6	5.1	1.5	5.1	ns
t_{PHL}	LEA, LEB to BPAR, APAR, Feed Thru Mode	1.5	3.6	5.1	1.5	5.1	
t_{PLH}	Propagation Delay	1.6	5.4	8.4	1.6	8.4	ns
t_{PHL}	LEA, LEB to $\overline{ERRA}$, $\overline{ERRB}$	1.6	5.4	8.4	1.6	8.4	
t_{PZH}	Output Enable Time	1.5	3.6	6.0	1.5	6.0	ns
t_{PZL}	$\overline{GBA}$ or $\overline{GAB}$ to A_n, APAR or B_n, BPAR	1.5	3.4	6.0	1.5	6.0	
t_{PHZ}	Output Disable Time	1.0	4.0	6.0	1.0	6.0	ns
t_{PLZ}	$\overline{GBA}$ or $\overline{GAB}$ to A_n, APAR or B_n, BPAR	1.0	3.3	6.0	1.0	6.0	
$t_{PLH}t_{PHL}$	Propagation Delay	1.5	3.3	5.4	1.5	5.4	ns
	APAR to BPAR, BPAR to APAR	1.5	3.8	5.4	1.5	5.4	

AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	3.0	5.3	1.5	5.3	ns
t_{PHL}	A_n, to B_n	1.5	3.5	5.3	1.5	5.3	
t_{PLH}	Propagation Delay	2.5	5.9	9.9	2.5	9.9	ns
t_{PHL}	A_n, B_n to BPAR, APAR	2.5	5.8	9.9	2.5	9.9	
t_{PLH}	Propagation Delay	2.5	5.4	9.4	2.5	9.4	ns
t_{PHL}	A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$	2.5	5.4	9.4	2.5	9.4	
t_{PLH}	Propagation Delay	1.5	3.7	6.5	1.5	6.5	ns
t_{PHL}	APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$	1.5	3.7	6.5	1.5	6.5	
t_{PLH}	Propagation Delay	2.0	4.4	7.4	2.0	7.4	ns
t_{PHL}	ODD/EVEN to APAR, BPAR	2.0	4.4	7.4	2.0	7.4	
t_{PLH}	Propagation Delay	1.8	4.0	6.5	1.8	6.5	ns
t_{PHL}	ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$	1.8	4.0	6.5	1.8	6.5	
t_{PLH}	Propagation Delay	1.5	3.8	6.5	1.5	6.5	ns
t_{PHL}	SEL to APAR, BPAR	1.5	3.8	6.5	1.5	6.5	
t_{PLH}	Propagation Delay	1.5	3.2	5.1	1.5	5.1	ns
t_{PHL}	LEA, LEB to B_n, A_n	1.5	3.2	5.1	1.5	5.1	
t_{PLH}	Propagation Delay	2.5	5.9	9.2	2.5	9.2	
t_{PHL}	LEA, LEB to BPAR, APAR	2.5	5.7	9.2	2.5	9.2	ns
	Generate Mode						
t_{PLH}	Propagation Delay	1.5	3.6	5.6	1.5	5.6	ns
t_{PHL}	LEA, LEB to BPAR, APAR,	1.5	3.6	5.6	1.5	5.6	
	Feed Thru Mode						
t_{PLH}	Propagation Delay	1.6	5.4	8.9	1.6	8.9	ns
t_{PHL}	LEA, LEB to $\overline{ERRA}$, $\overline{ERRB}$	1.6	5.4	8.9	1.6	8.9	
t_{PZH}	Output Enable Time	1.5	3.6	6.5	1.5	6.5	ns
t_{PZL}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.5	3.4	6.5	1.5	6.5	
	APAR or B_n, BPAR						
t_{PHZ}	Output Disable Time	1.0	4.0	6.5	1.0	6.5	ns
t_{PLZ}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.0	3.3	6.5	1.0	6.5	
	APAR or B_n, BPAR						
t_{PLH}	Propagation Delay	1.5	3.3	5.9	1.5	5.9	ns
t_{PHL}	APAR to BPAR, BPAR to APAR	1.5	3.8	5.9	1.5	5.9	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW A_n,	1.5		1.5		ns
$t_S(L)$	APAR to LEA or B_n, BPAR to LEB	1.5		1.5		
$t_H(H)$	Hold Time, HIGH or LOW A_n,	1.0		1.0		ns
$t_H(L)$	APAR to LEA or B_n, BPAR to LEB	1.0		1.0		
$t_W(H)$	Pulse Width, HIGH	3.0		3.0		ns
	LEA or LEB					

Extended AC Electrical Characteristics

(SOIC and PLCC Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, 9 Outputs Switching (Note 9)			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 10)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 9 Outputs Switching (Note 11)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		6.2	2.0	7.2	2.5	9.5	ns
t_{PHL}	A_n to B_n	1.5		6.2	2.0	7.2	2.5	9.5	
t_{PLH}	Propagation Delay	1.5		6.8	2.0	8.0	2.5	10.0	ns
t_{PHL}	APAR to BPAR	1.5		6.8	2.0	8.0	2.0	10.0	
t_{PLH}	Propagation Delay	2.5		10.0	3.0	12.5	3.5	13.5	ns
t_{PHL}	A_n, B_n to BPAR, APAR	2.5		10.0	3.0	12.5	3.5	13.5	
t_{PLH}	Propagation Delay		(Note 13)		3.0	12.0		(Note 13)	ns
t_{PHL}	A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$				3.0	12.0			
t_{PLH}	Propagation Delay		(Note 13)		2.0	9.0		(Note 13)	ns
t_{PHL}	APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$				2.0	9.0			
t_{PLH}	Propagation Delay		(Note 13)		2.5	9.9		(Note 13)	ns
t_{PHL}	ODD/EVEN to APAR, BPAR				2.5	9.9			
t_{PLH}	Propagation Delay		(Note 13)		2.0	8.8		(Note 13)	ns
t_{PHL}	ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$				2.0	8.8			
t_{PLH}	Propagation Delay		(Note 13)		2.0	9.5		(Note 13)	ns
t_{PHL}	SEL to APAR, BPAR				2.0	9.5			
t_{PLH}	Propagation Delay	1.5		5.7	2.0	7.9	2.5	10.0	ns
t_{PHL}	LEA, LEB to B_n, A_n	1.5		5.7	2.0	7.9	2.5	10.0	
t_{PLH}	Propagation Delay	1.5		9.5	2.0	12.0	2.5	13.0	ns
t_{PHL}	LEA, LEB to BPAR, APAR	1.5		9.5	2.0	12.0	2.5	13.0	
t_{PLH}	Propagation Delay		(Note 13)		2.0	11.5		(Note 13)	ns
t_{PHL}	LEA, LEB to $\overline{ERRA}$, $\overline{ERRB}$				2.0	11.5			
t_{PZH}	Output enable time	1.5		7.0	2.0	8.5	2.5	10.5	
t_{PZL}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.5		7.0	2.0	8.5	2.5	10.5	ns
	APAR or B_n, BPAR								
t_{PHZ}	Output disable time	1.0		6.5					
t_{PLZ}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.0		6.5	(Note 12)		(Note 12)		ns
	APAR or B_n, BPAR								

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load

Note 12: The 3-STATE delay time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 13: Not applicable for multiple output switching.

Extended AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, 9 Outputs Switching (Note 14)			$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 1 Output Switching (Note 15)		$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 250$ pF, 9 Outputs Switching (Note 16)		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{TOGGLE}	Max Toggle Frequency		100						MHz
t_{PLH}	Propagation Delay	1.5		6.7	2.0	7.7	2.5	10.1	ns
t_{PHL}	A_n to B_n	1.5		6.7	2.0	7.7	2.5	10.1	
t_{PLH}	Propagation Delay	1.5		7.3	2.0	8.5	2.5	10.6	ns
t_{PHL}	APAR to BPAR	1.5		7.3	2.0	8.5	2.0	10.6	
t_{PLH}	Propagation Delay	2.5		10.7	3.0	13.2	3.5	14.3	ns
t_{PHL}	A_n, B_n to BPAR, APAR	2.5		10.7	3.0	13.2	3.5	14.3	
t_{PLH}	Propagation Delay		(Note 18)		3.0	12.9	(Note 18)		ns
t_{PHL}	A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$				3.0	12.9			
t_{PLH}	Propagation Delay		(Note 18)		2.0	9.5	(Note 18)		ns
t_{PHL}	APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$				2.0	9.5			
t_{PLH}	Propagation Delay		(Note 18)		2.5	10.4	(Note 18)		ns
t_{PHL}	ODD/EVEN to APAR, BPAR				2.5	10.4			
t_{PLH}	Propagation Delay		(Note 18)		2.0	9.3	(Note 18)		ns
t_{PHL}	ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$				2.0	9.3			
t_{PLH}	Propagation Delay		(Note 18)		2.0	10.0	(Note 18)		ns
t_{PHL}	SEL to APAR, BPAR				2.0	10.0			
t_{PLH}	Propagation Delay	1.5		6.2	2.0	8.4	2.5	10.6	ns
t_{PHL}	LEA, LEB to B_n, A_n	1.5		6.2	2.0	8.4	2.5	10.6	
t_{PLH}	Propagation Delay	1.5		10.0	2.0	12.5	2.5	13.6	ns
t_{PHL}	LEA, LEB to BPAR, APAR	1.5		10.0	2.0	12.5	2.5	13.6	
t_{PLH}	Propagation Delay		(Note 18)		2.0	12.0	(Note 18)		ns
t_{PHL}	LEA, LEB to $\overline{ERRA}$, $\overline{ERRB}$				2.0	12.0			
t_{PZH}	Output enable time	1.5		7.5	2.0	9.0	2.5	11.1	
t_{PZL}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.5		7.5	2.0	9.0	2.5	11.1	ns
	APAR or B_n, BPAR								
t_{PHZ}	Output disable time	1.0		7.0					
t_{PLZ}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.0		7.0	(Note 17)		(Note 17)		ns
	APAR or B_n, BPAR								

Note 14: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 15: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 16: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load

Note 17: The 3-STATE delay time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 18: Not applicable for multiple output switching.

Skew

(PLCC package) (Note 2)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 50$ pF 9 Outputs Switching (Note 19)	$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.5V–5.5V$ $C_L = 250$ pF 9 Outputs Switching (Note 20)	Units
		Max	Max	
t_{OSHL} (Note 21)	Pin to Pin Skew HL Transitions	1.0	2.0	ns
t_{OSLH} (Note 21)	Pin to Pin Skew LH Transitions	1.1	2.1	ns
t_{PS} (Note 22)	Duty Cycle LH–HL Skew	2.0	3.5	ns
t_{OST} (Note 21)	Pin to Pin Skew LH/HL Transitions	2.0	3.5	ns
t_{PV} (Note 23)	Device to Device Skew LH/HL Transitions	3.0	4.0	ns

Note 19: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 20: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 21: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}). This specification is guaranteed but not tested. Skew applies to propagation delays individually; i.e., A_n to B_n separate from LEA to A_n.

Note 22: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

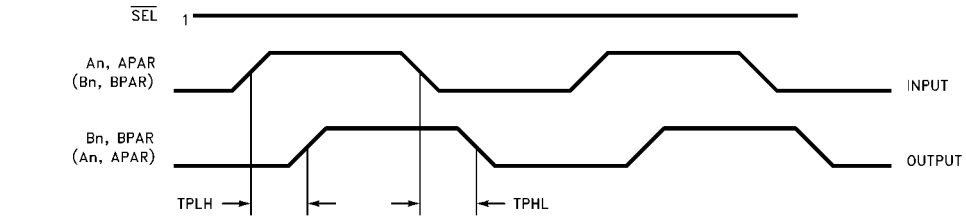
Note 23: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Pin Capacitance	5.0	pF	$V_{CC} = 0V$
$C_{I/O}$ (Note 24)	Output Capacitance	11.0	pF	$V_{CC} = 5.0V$

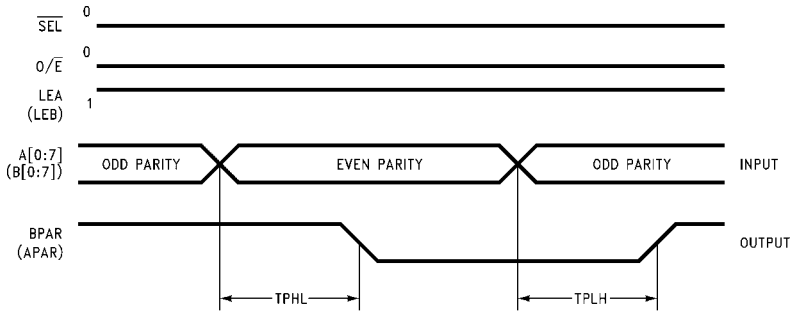
Note 24: $C_{I/O}$ is measured at frequency, f = 1 MHz, per MIL-STD-883B, Method 3012.

AC Path



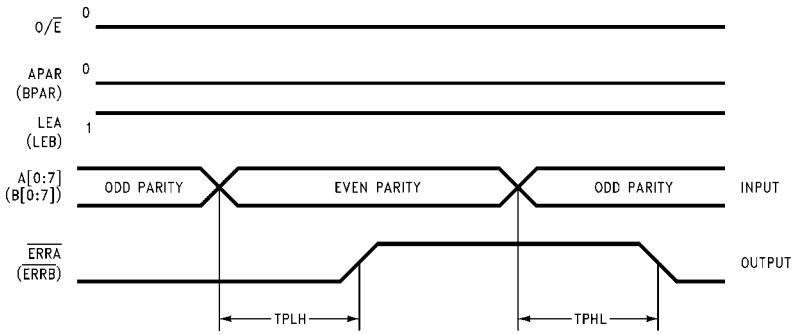
A_n, APAR → B_n, BPAR
(B_n, BPAR → A_n, APAR)

FIGURE 1.



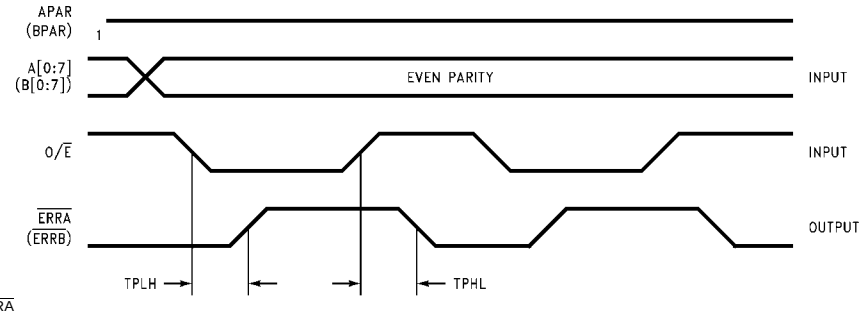
A_n → BPAR
(B_n → APAR)

FIGURE 2.



A_n → $\overline{ERRA}$
(B_n → $\overline{ERRB}$)

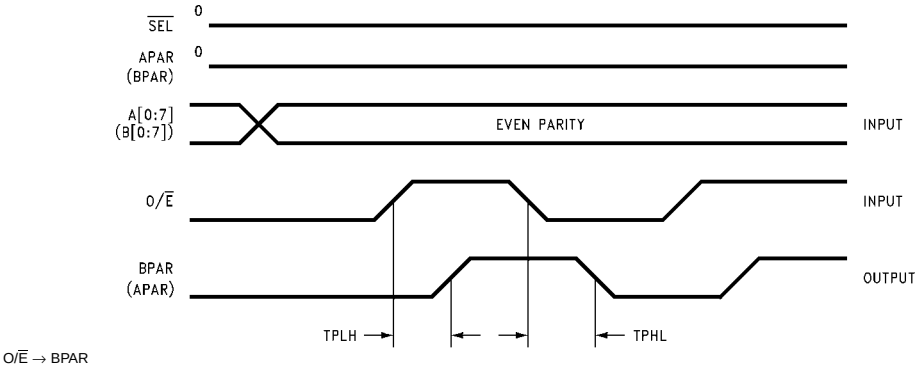
FIGURE 3.



O/$\overline{E}$ → $\overline{ERRA}$
O/$\overline{E}$ → $\overline{ERRB}$

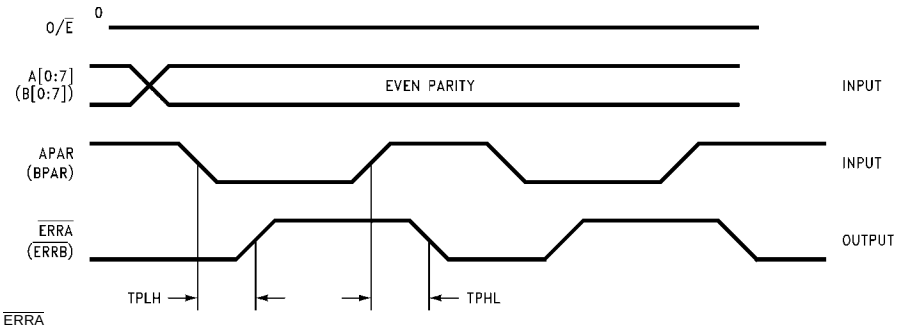
FIGURE 4.

AC Path (Continued)



O/E → BPAR
(O/E → APAR)

FIGURE 5.



APAR → ERRA
(BPAR → ERRB)

FIGURE 6.

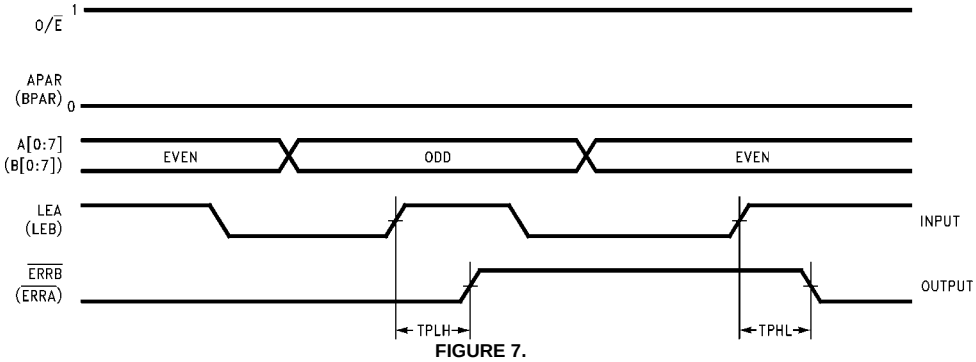
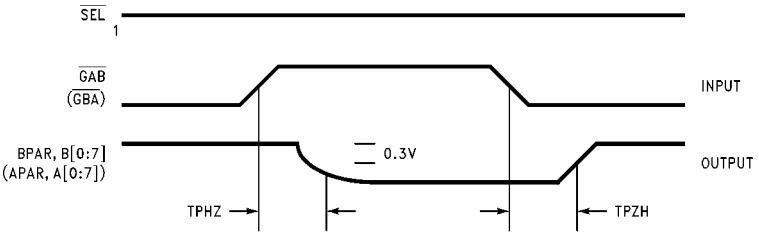


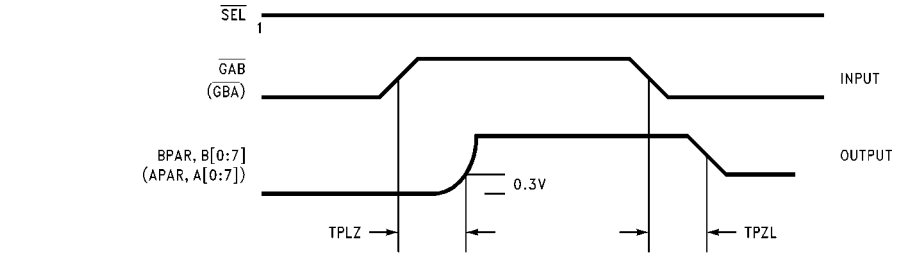
FIGURE 7.



ZH, HZ

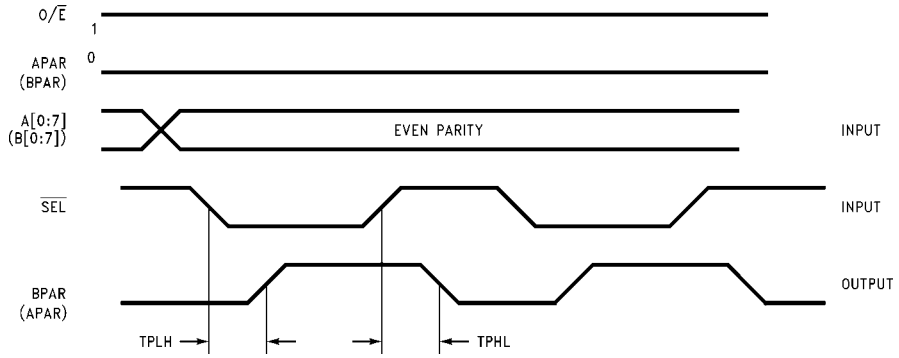
FIGURE 8.

AC Path (Continued)



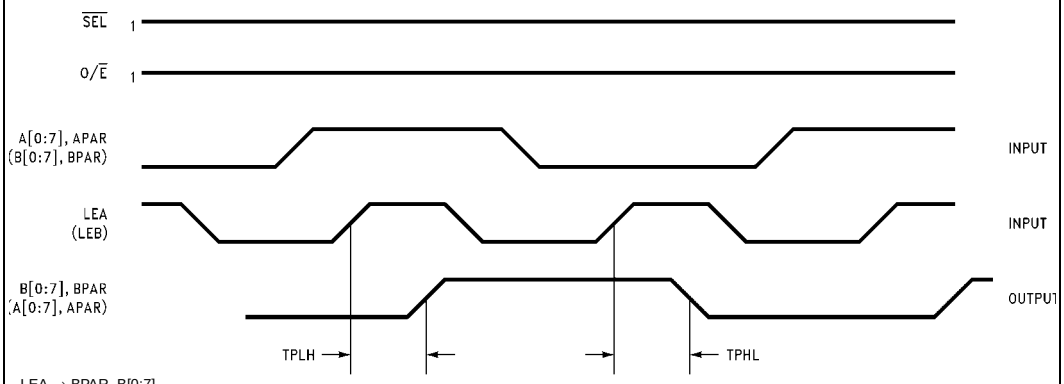
ZL, LZ

FIGURE 9.



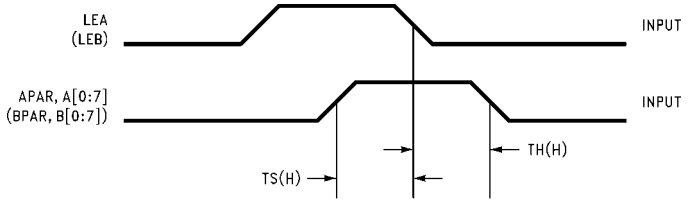
SEL → BPAR
(SEL → APAR)

FIGURE 10.



LEA → BPAR, B[0:7]
(LEB → APAR, A[0:7])

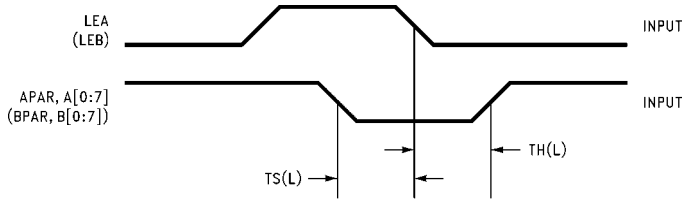
FIGURE 11.



TS(H), TH(H)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 12.

AC Path (Continued)



TS(L), TH(L)

LEA → APAR, A[0:7]

(LEB → BPAR, B[0:7])

FIGURE 13.

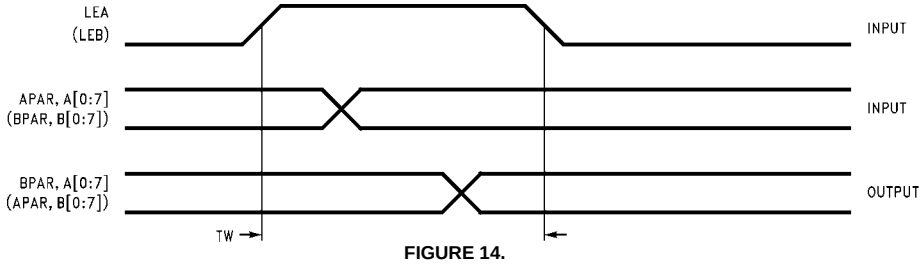
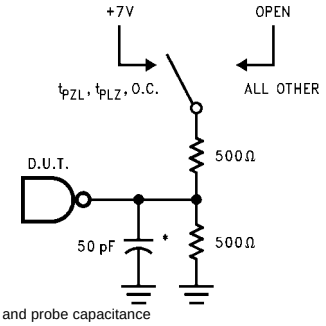


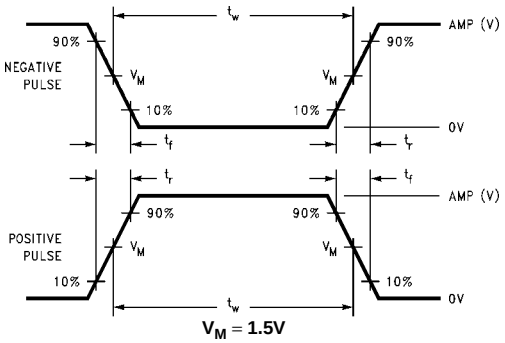
FIGURE 14.

AC Loading



*Includes jig and probe capacitance

FIGURE 15. Standard AC Test Load



V_M = 1.5V

FIGURE 16.

Input Pulse Requirements

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 17. Test Input Signal Requirements

AC Waveforms

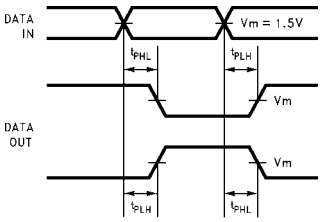


FIGURE 18. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

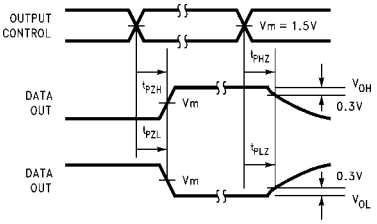


FIGURE 20. 3-STATE Output HIGH and LOW Enable and Disable Times

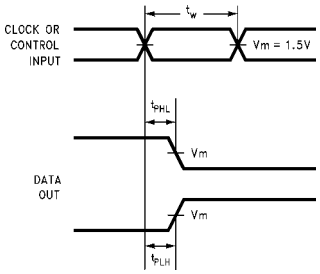


FIGURE 19. Propagation Delay, Pulse Width Waveforms

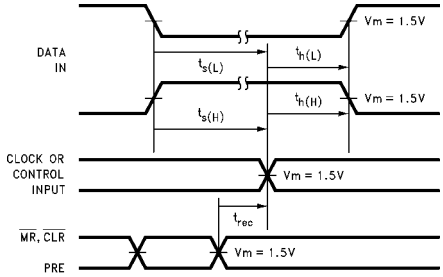
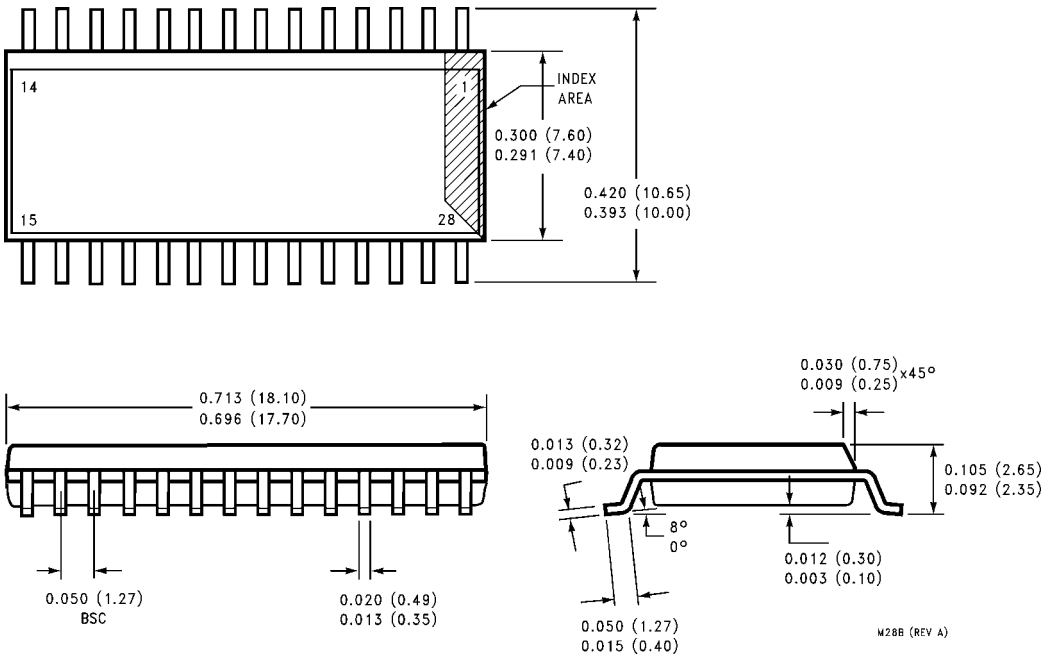
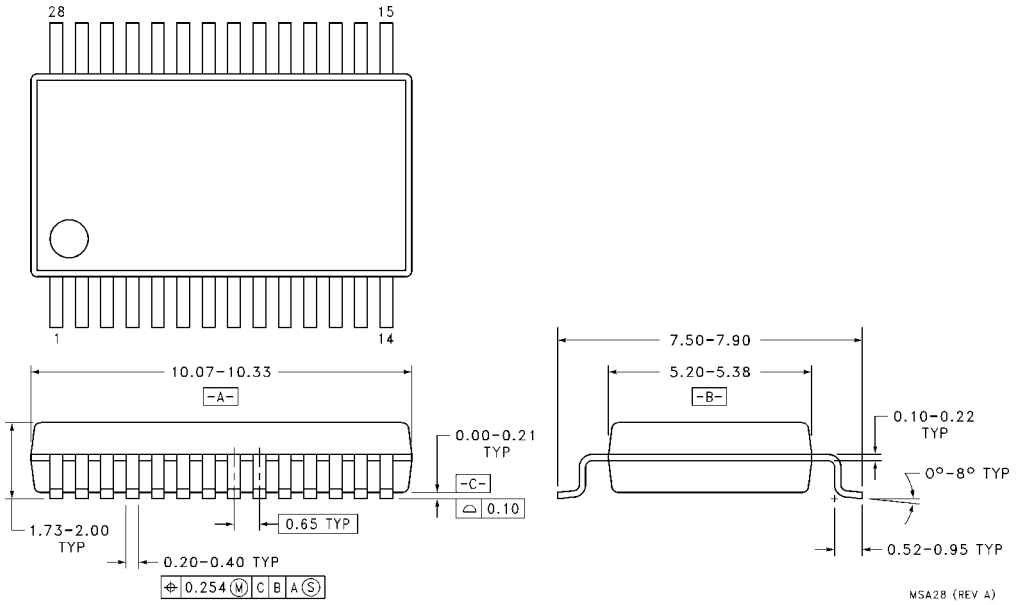


FIGURE 21. Setup Time, Hold Time and Recovery Time Waveforms

Physical Dimensions inches (millimeters) unless otherwise noted

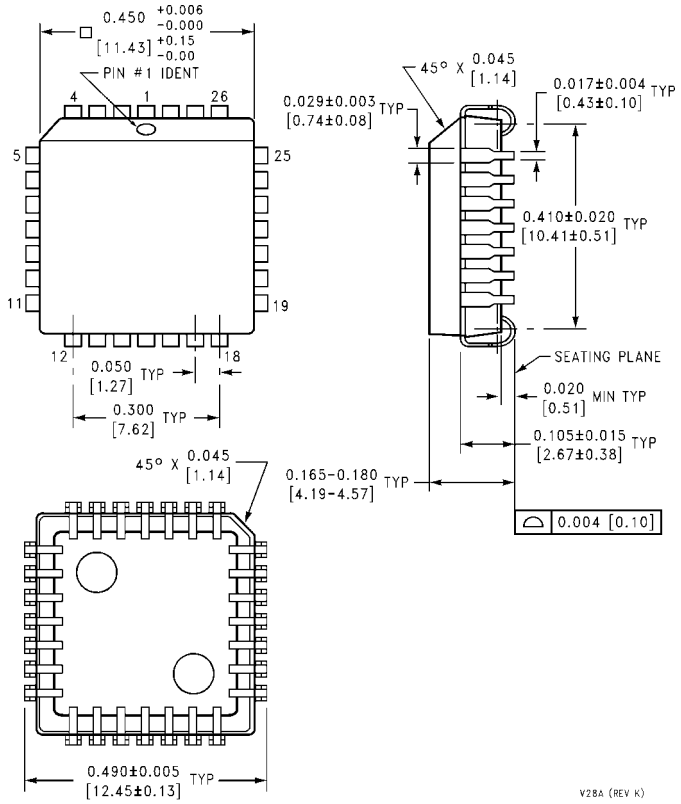


28-Lead Small Outline Integrated Circuit (SOIC), MS-013, 0.300" Wide Body
Package Number M28B



28-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA28

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450" Square
Package Number V28A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC00 • 74ACT00
Quad 2-Input NAND Gate

General Description

The AC/ACT00 contains four 2-input NAND gates.

Features

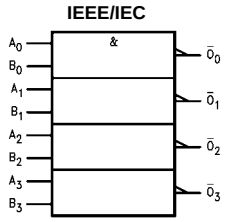
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- ACT00 has TTL-compatible inputs

Ordering Code:

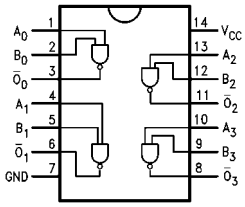
Order Number	Package Number	Package Description
74AC00SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ Type II, 5.3mm Wide
74AC00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC00PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT00SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ Type II, 5.3mm Wide
74ACT00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT00PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering form. (PC not available in Tape and Reel.)

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 3)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 3)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC}	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	2.0	7.0	9.5	2.0	10.0	ns
		5.0	1.5	6.0	8.0	1.5	8.5	
t_{PHL}	Propagation Delay	3.3	1.5	5.5	8.0	1.0	8.5	ns
		5.0	1.5	4.5	6.5	1.0	7.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

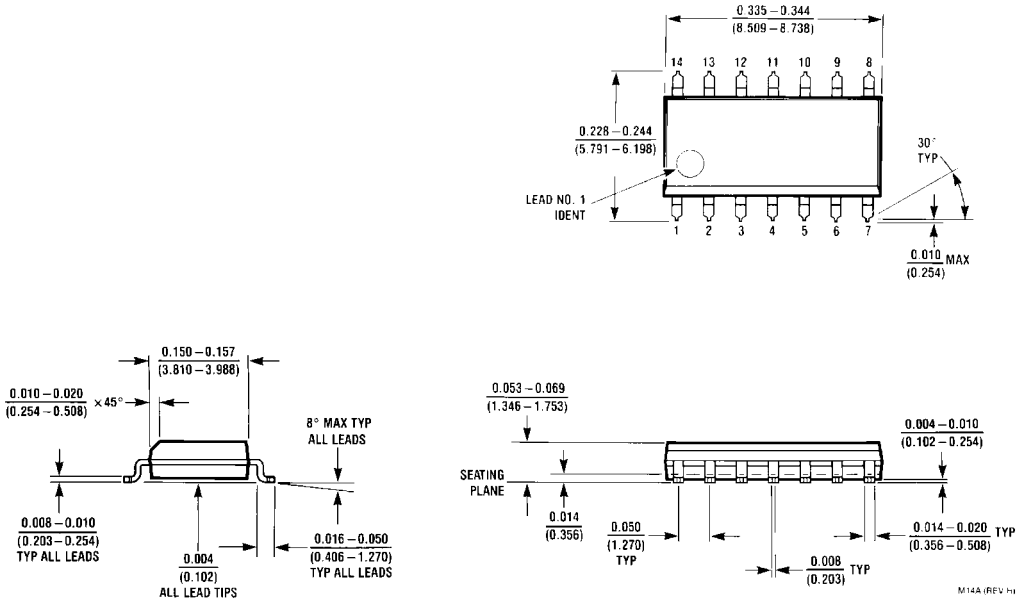
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	1.5	5.5	9.0	1.0	9.5	ns
t_{PHL}	Propagation Delay	5.0	1.5	4.0	7.0	1.0	8.0	ns

Note 8: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

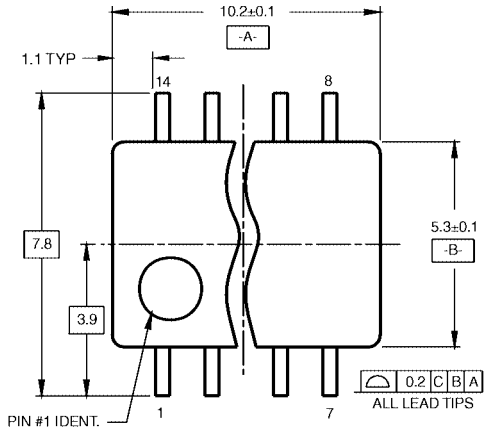
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance	30.0	pF	$V_{CC} = 5.0V$

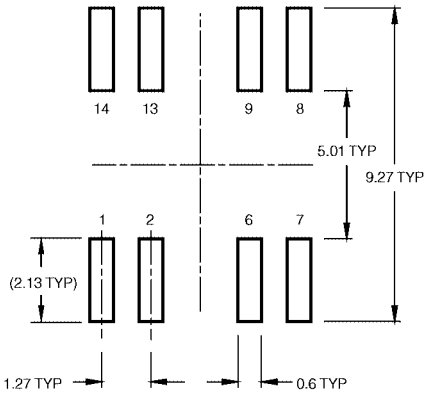
Physical Dimensions inches (millimeters) unless otherwise noted



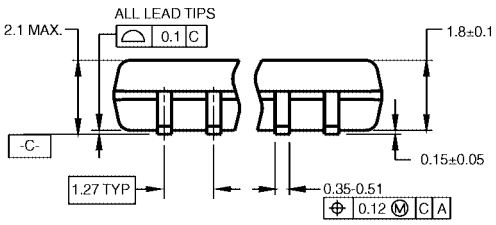
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

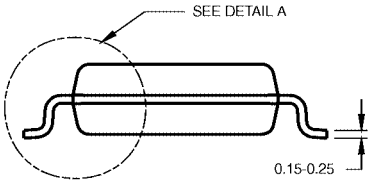
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



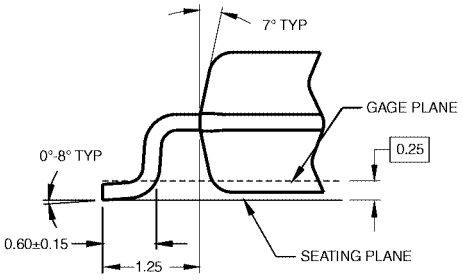


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

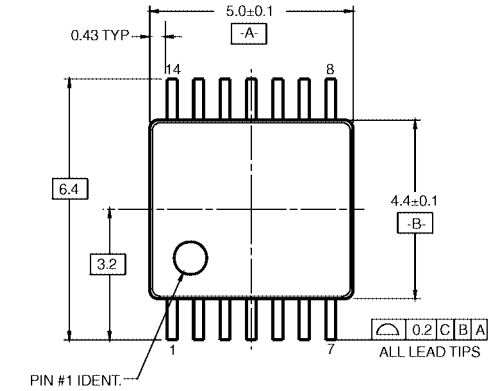
B. DIMENSIONS ARE IN MILLIMETERS.

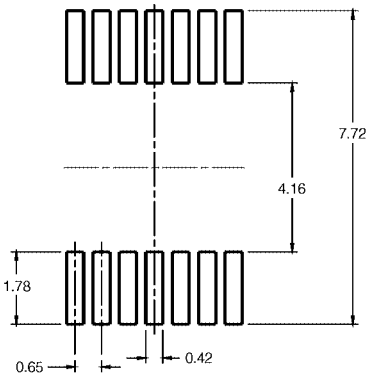
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

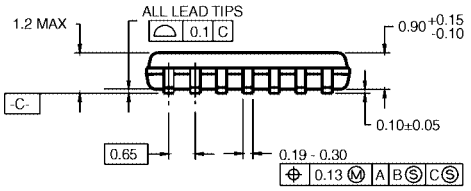
14-Lead Small Outline Package (SOIC), EIAJ Type II, 5.3mm Wide
Package Number M14D

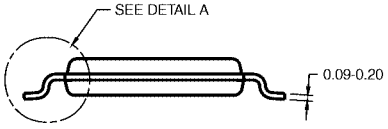
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

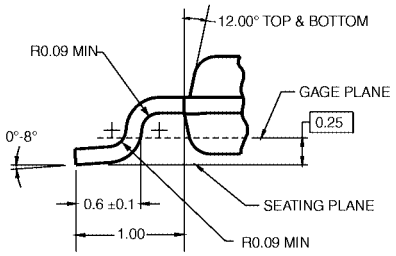




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

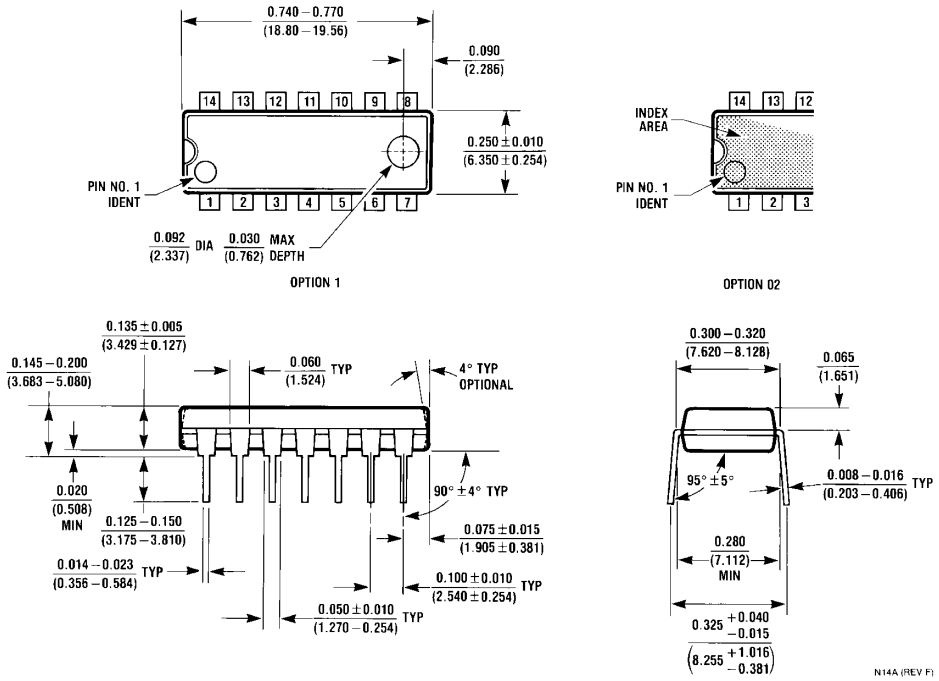
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153,4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC02•74ACT02
Quad 2-Input NOR Gate

General Description

The AC02/ACT02 contains four, 2-input NOR gates.

Features

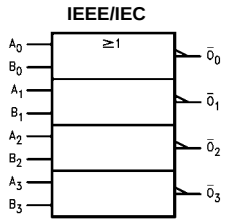
- I_{CC} reduced by 50% on 74AC02 only
- Outputs source/sink 24 mA
- ACT02 has TTL-compatible inputs

Ordering Codes:

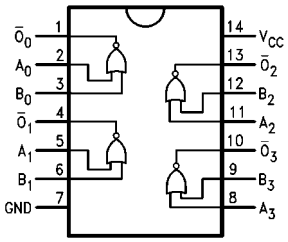
Order Number	Package Number	Package Description
74AC02SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC02PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT02SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT02PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. (PC not available in Tape and Reel.)

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or	
Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per	
Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL}= 24 mA
		5.5		0.36	0.44		I_{OL}= 24 mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, C_L = 50 pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, C_L = 50 pF Min	Max	Units
t_{PLH}	Propagation Delay	3.3	1.5	5.0	7.5	1.0	8.0	ns
		5.0	1.5	4.0	6.0	1.0	6.5	
t_{PHL}	Propagation Delay	3.3	1.5	5.0	7.5	1.0	8.0	ns
		5.0	1.5	4.5	6.5	1.0	7.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

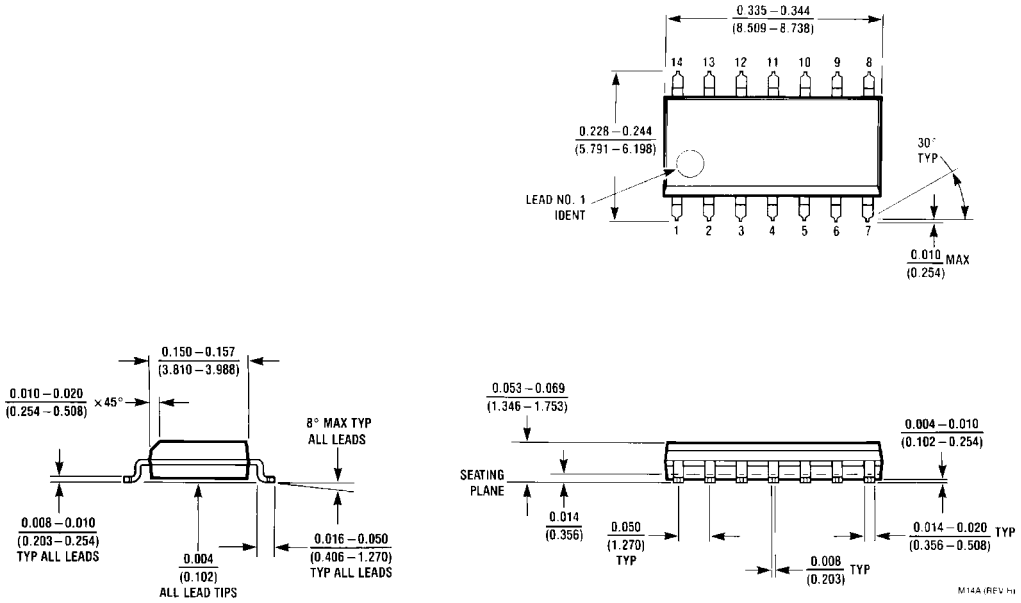
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, C_L = 50 pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, C_L = 50 pF Min	Max	Units
t_{PLH}	Propagation Delay	5.0	1.0	6.0	8.5	1.0	9.0	ns
t_{PHL}	Propagation Delay	5.0	1.0	6.5	9.5	1.0	10.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

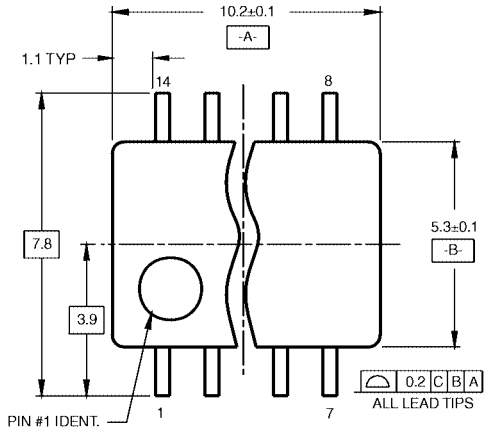
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	30.0	pF	V_{CC} = 5.0V

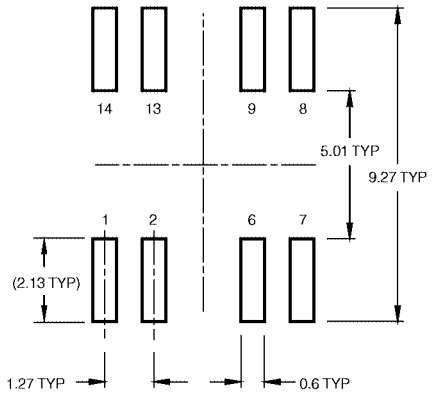
Physical Dimensions inches (millimeters) unless otherwise noted



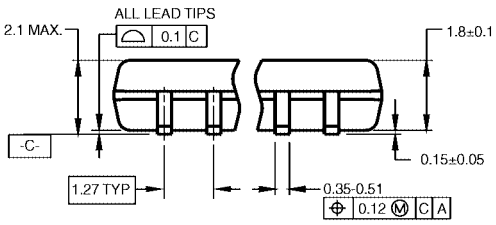
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

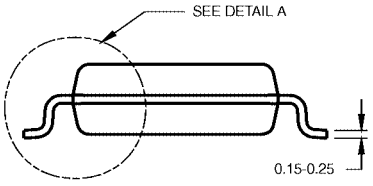
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



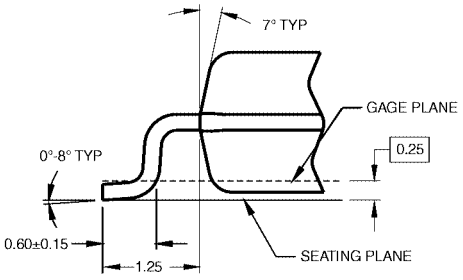


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

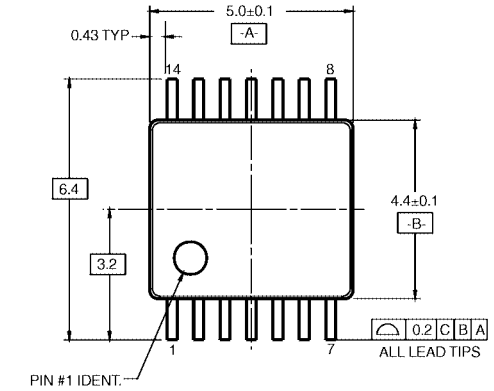
B. DIMENSIONS ARE IN MILLIMETERS.

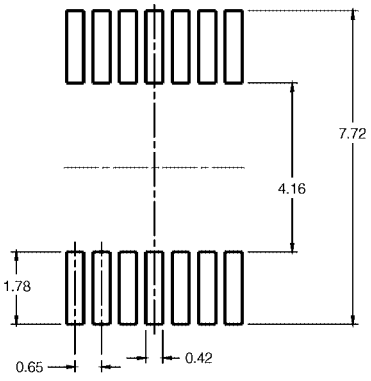
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

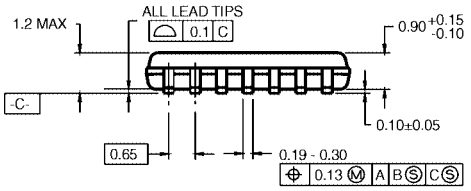
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

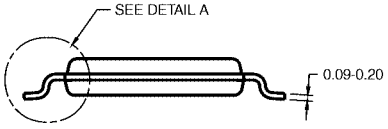
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

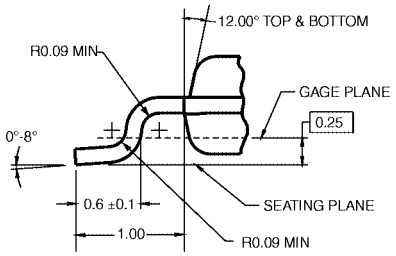




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

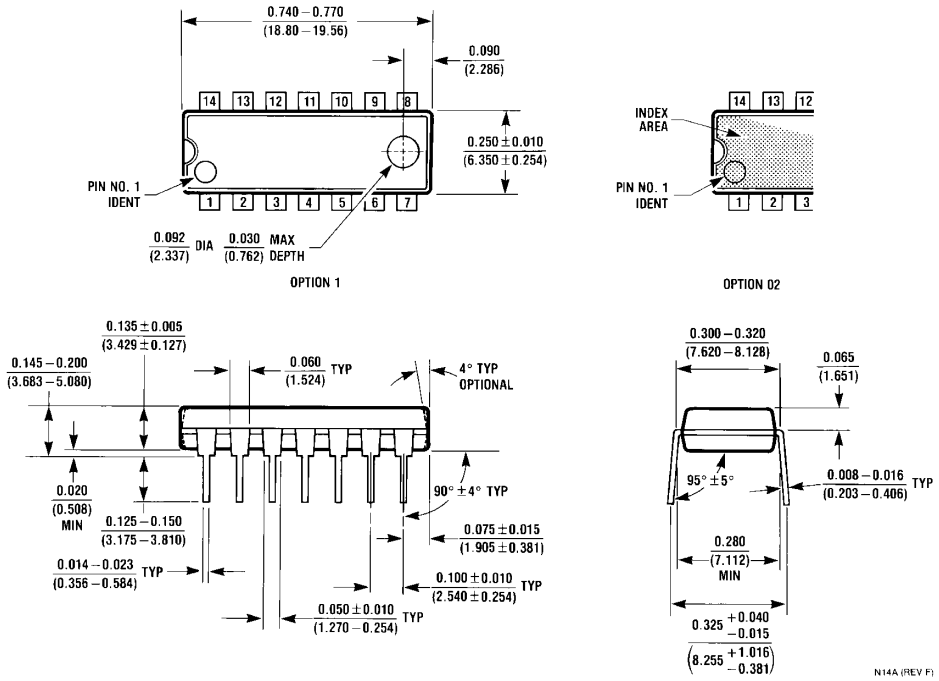
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP) JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC04 • 74ACT04
Hex Inverter

General Description

The AC/ACT04 contains six inverters.

Features

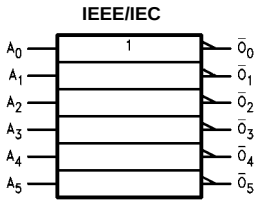
- I_{CC} reduced by 50% on 74AC only
- Outputs source/sink 24 mA
- ACT04 has TTL-compatible inputs

Ordering Code:

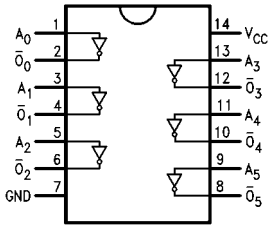
Order Number	Package Number	Package Description
74AC04SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC04PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT04SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT04PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. (PC not available in Tape and Reel.)

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL}= 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL}0 = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ p			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	4.5	9.0	1.0	10.0	ns
		5.0	1.5	4.0	7.0	1.0	7.5	
t_{PHL}	Propagation Delay	3.3	1.5	4.5	8.5	1.0	9.5	ns
		5.0	1.5	3.5	6.5	1.0	7.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

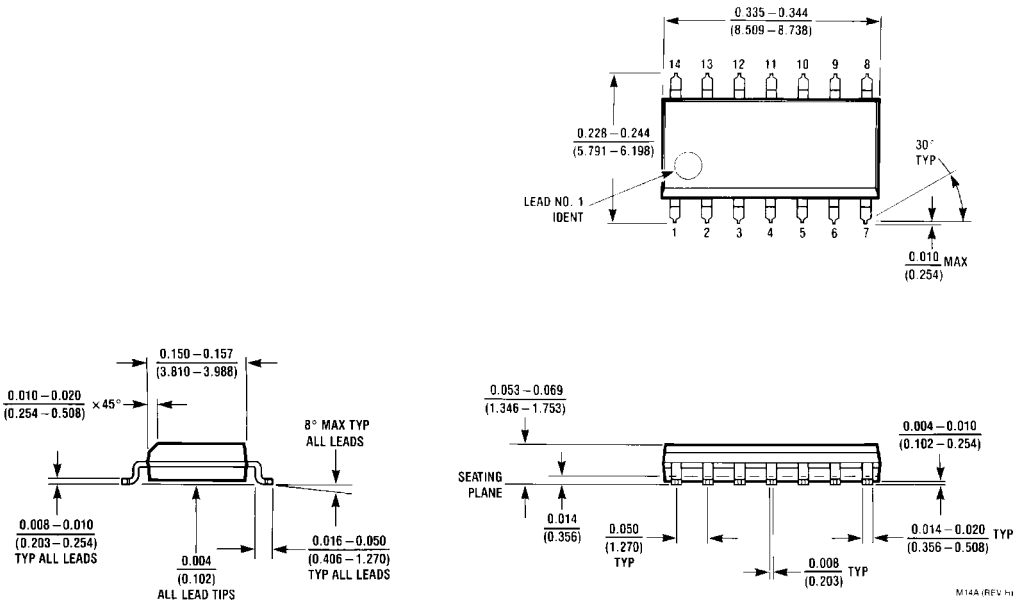
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	1.0	6.0	8.5	1.0	9.0	ns
t_{PHL}	Propagation Delay	5.0	1.0	5.5	8.0	1.0	8.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

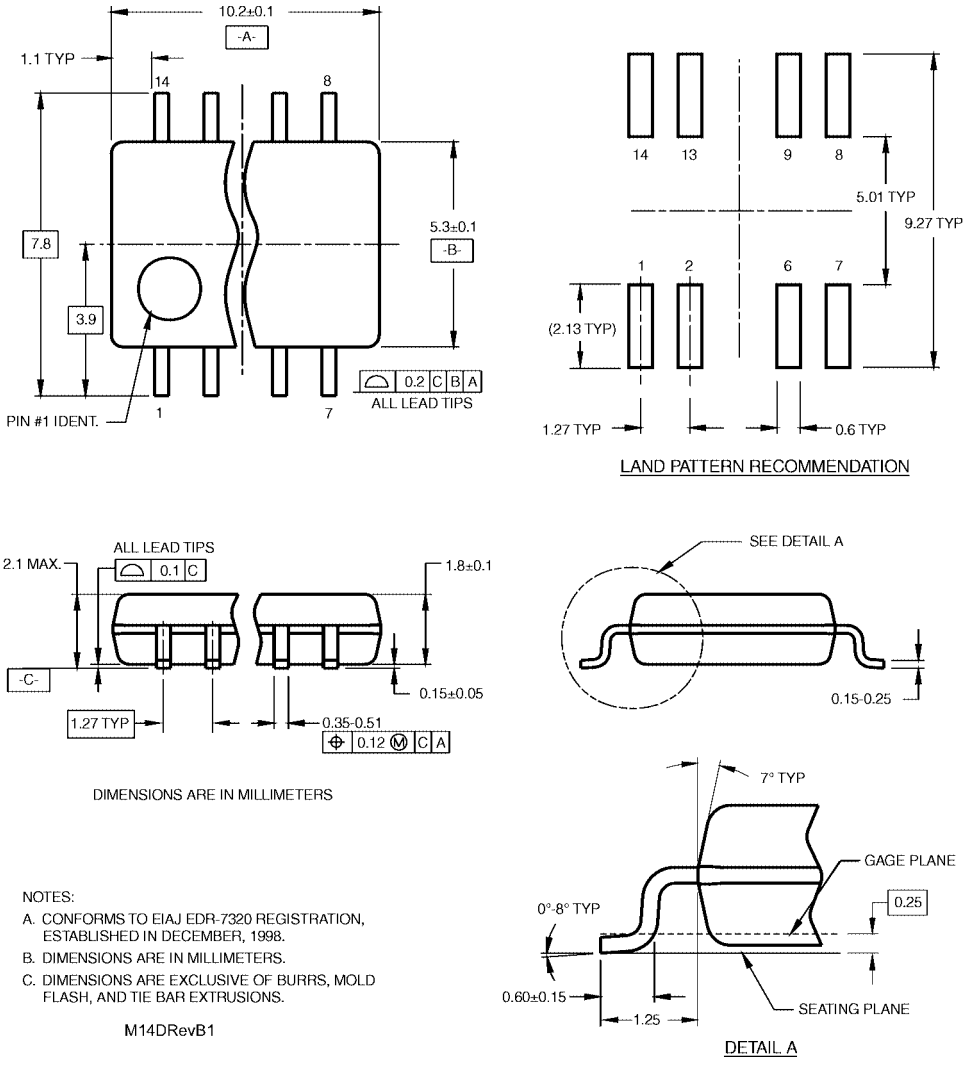
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
V_{CC}	Power Dissipation Capacitance	30.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

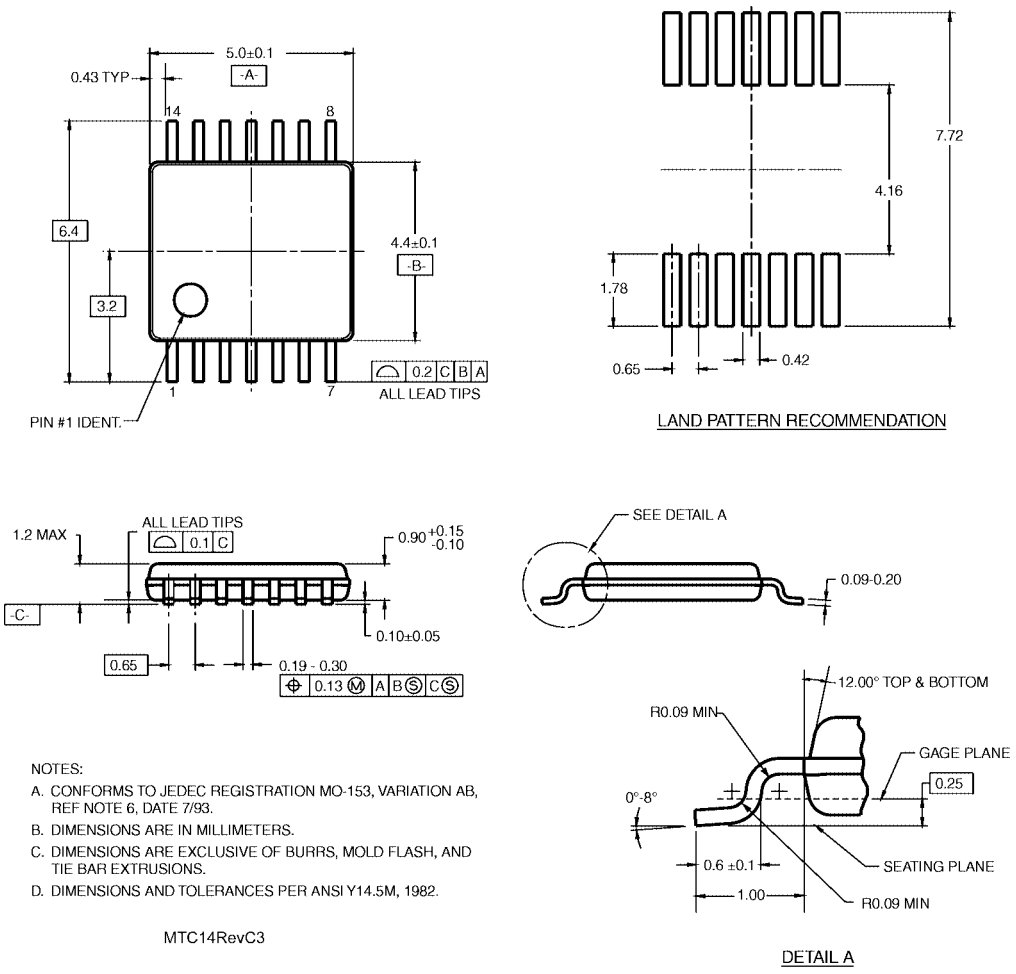
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

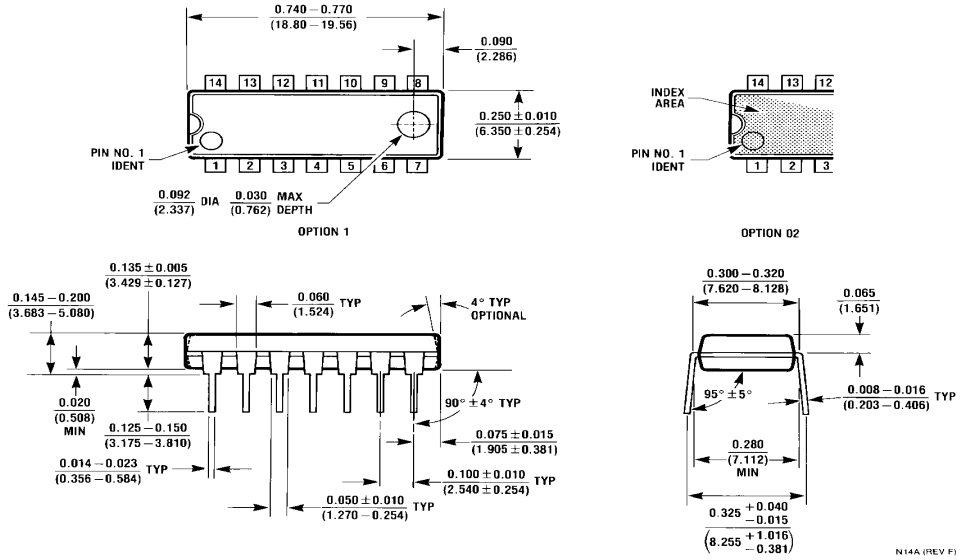
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1991
Revised December 1999

74AC05
Hex Inverter with Open Drain Outputs

General Description

The AC05 contains six inverters.

Features

- Outputs sink 24 mA
- Open drain for wired NOR function
- Radiation tolerant FACT™ process

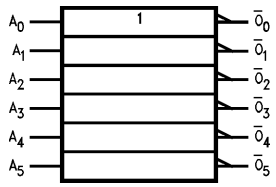
Ordering Code:

Order Number	Package Number	Package Description
74AC05SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body

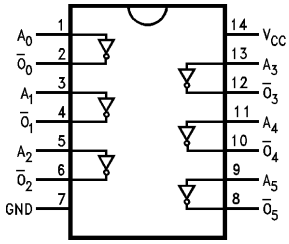
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.32	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OHD}	Off-State Current	5.5		+0.5	+10.0	μA	V_{IN} = V_{CC}
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5		50	75	mA	V_{OLD} = 1.65V Max
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$		Units
			Min	Max	Min	Min	
t_{PLZ}	Propagation Delay	3.3	2.0	14.5	2.0	14.5	ns
	(Note 6)	5.0	2.0	14.0	2.0	14.0	
t_{PZL}	Propagation Delay	3.3	2.0	6.5	2.0	6.5	ns
		5.0	2.0	5.0	2.0	5.0	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

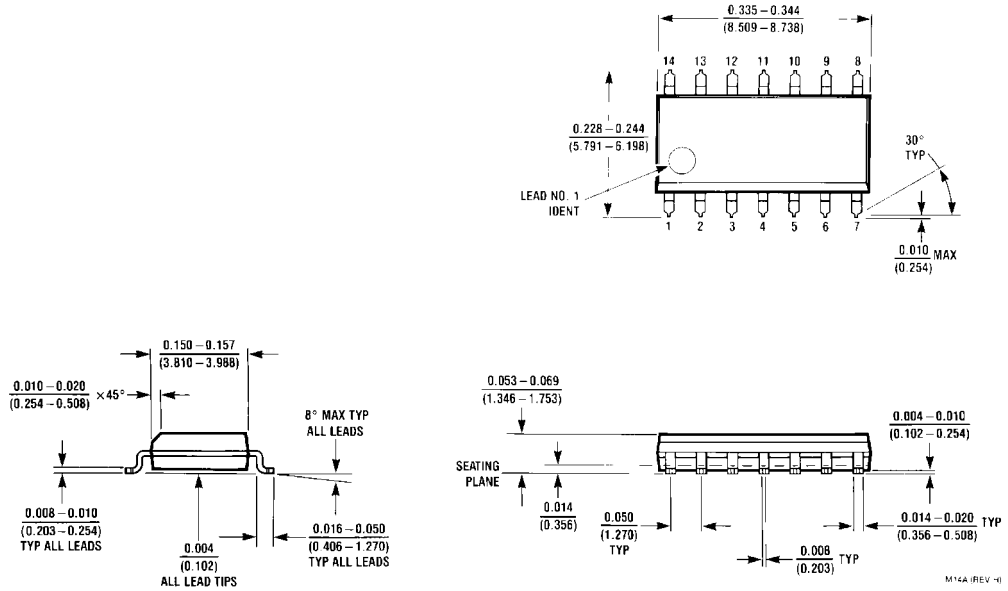
Note 6: AC Load is V_{CC} x 2, $R_L = 1\ k\Omega$

$C_L = 50$ pF

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30.0	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M14A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC08 • 74ACT08
Quad 2-Input AND Gate

General Description

The AC/ACT08 contains four, 2-input AND gates.

Features

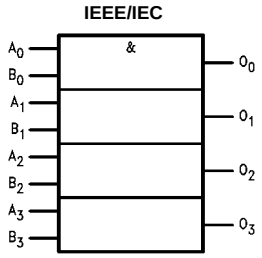
- I_{CC} reduced by 50% on 74AC only
- Outputs source/sink 24 mA

Ordering Code:

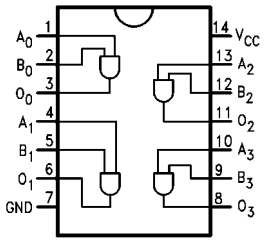
Order Number	Package Number	Package Description
74AC08SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC08SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC08PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT08SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT08PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. (PC not available in Tape and Reel.)

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay	3.3	1.5	7.5	9.5	1.0	10.0	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t_{PHL}	Propagation Delay	3.3	1.5	7.0	8.5	1.0	9.0	ns
		5.0	1.5	5.5	7.0	1.0	7.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

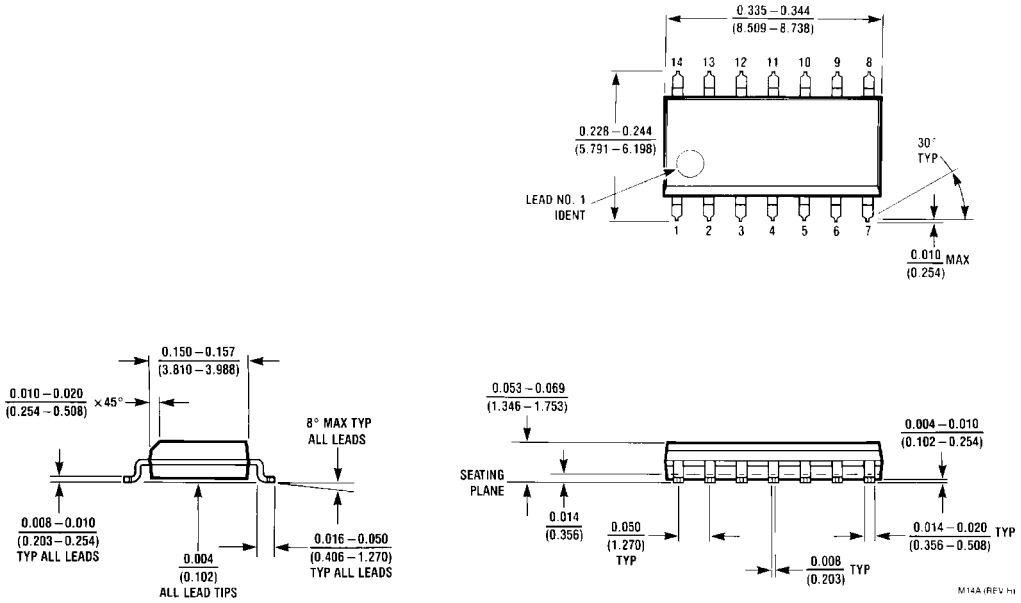
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns
t_{PHL}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

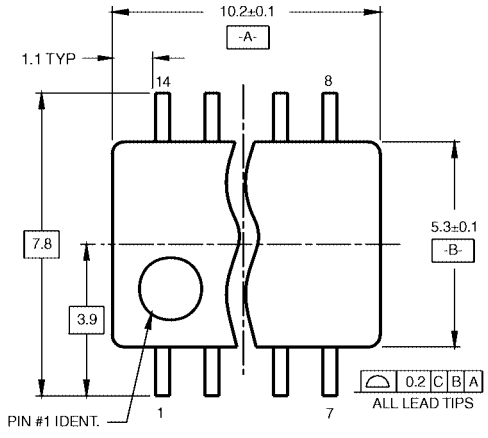
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	20.0	pF	$V_{CC} = 5.0V$

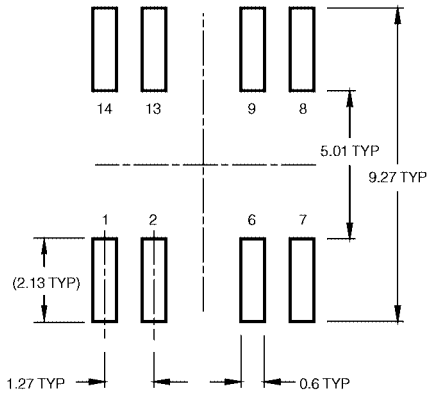
Physical Dimensions inches (millimeters) unless otherwise noted



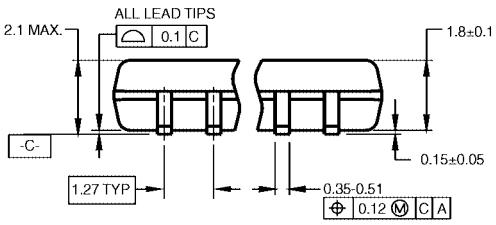
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

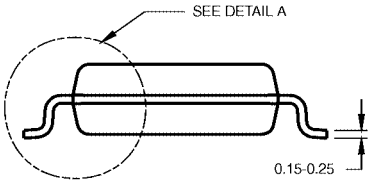
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

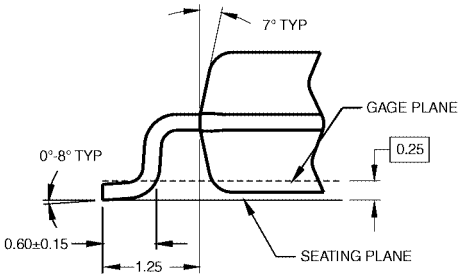
NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

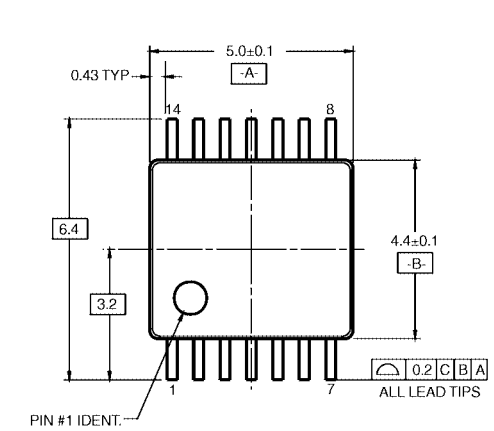
M14DRevB1

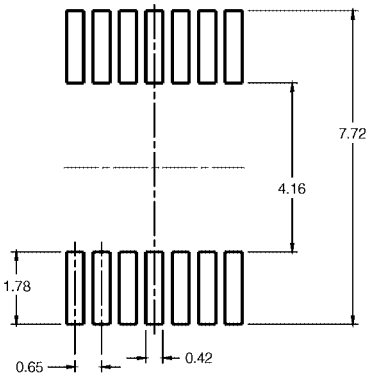


DETAIL A

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





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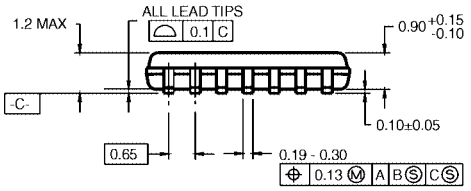
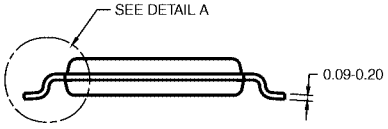
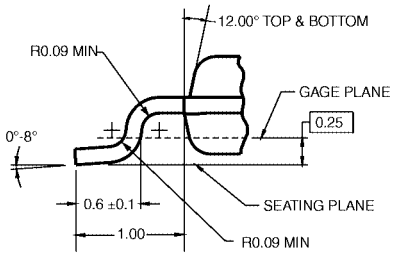






DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

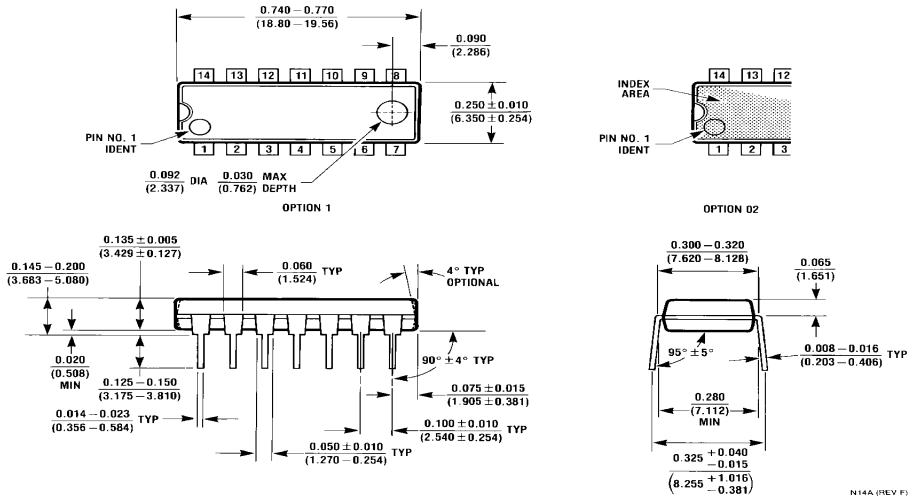
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised January 2000

74AC10 • 74ACT10
Triple 3-Input NAND Gate

General Description

The AC/ACT10 contains three, 3-input NAND gates.

Features

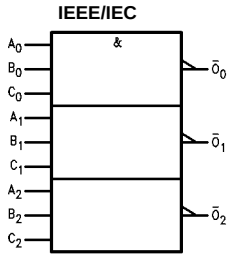
- I_{CC} reduced by 50% on 74AC only
- Outputs source/sink 24 mA

Ordering Code:

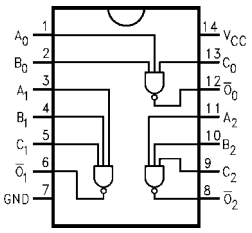
Order Number	Package Number	Package Description
74AC10SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC10SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC10MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC10PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT10SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT10PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n, C_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	6.0	9.5	1.0	10.5	ns
		5.0	1.5	4.5	7.0	1.0	8.0	
t_{PHL}	Propagation Delay	3.3	1.5	5.5	8.5	1.0	10.0	ns
		5.0	1.5	4.0	6.0	1.0	6.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

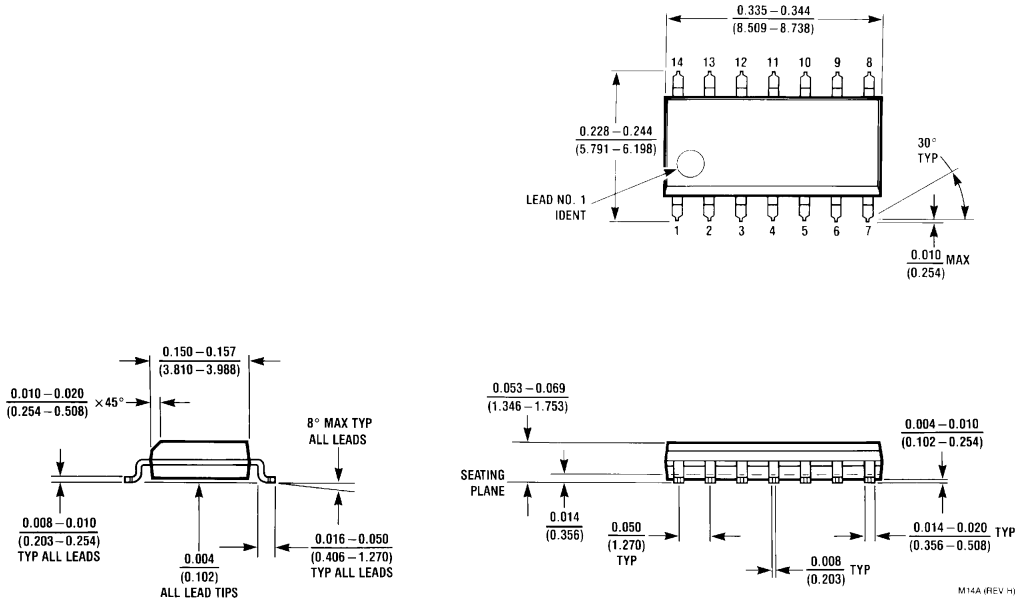
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns
t_{PHL}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	9.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

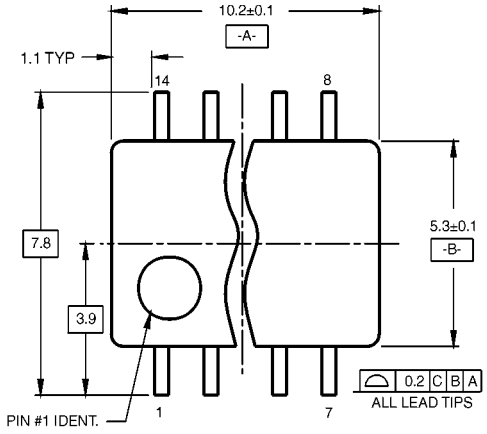
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	25.0	pF	$V_{CC} = 5.0V$

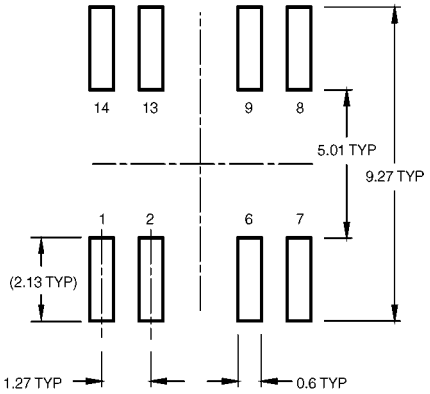
Physical Dimensions inches (millimeters) unless otherwise noted



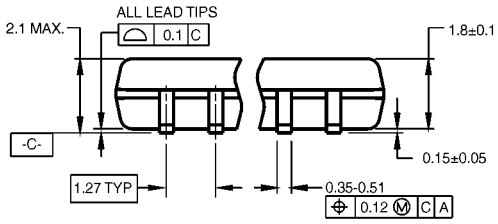
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number M14A

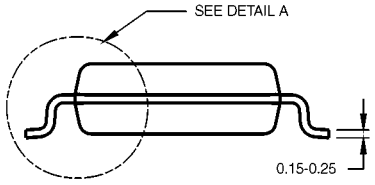
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



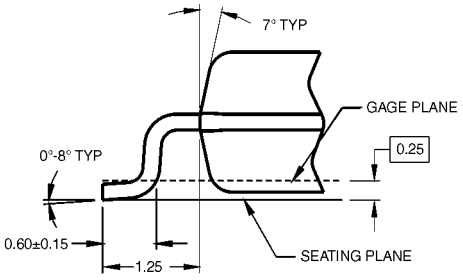


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

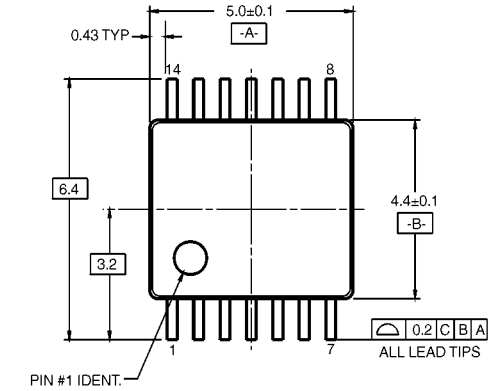
B. DIMENSIONS ARE IN MILLIMETERS.

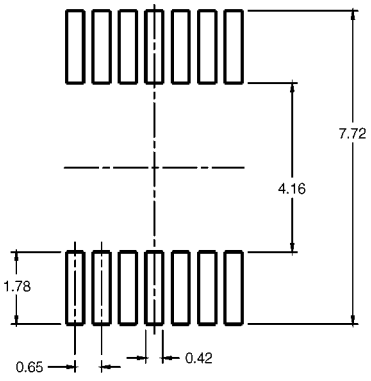
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

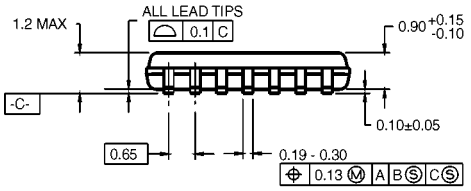
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

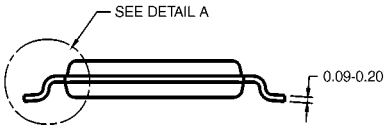
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

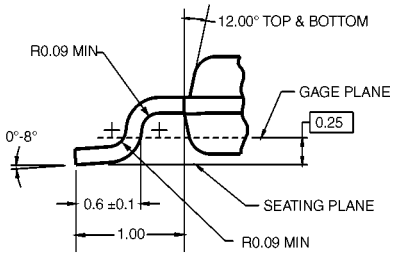




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

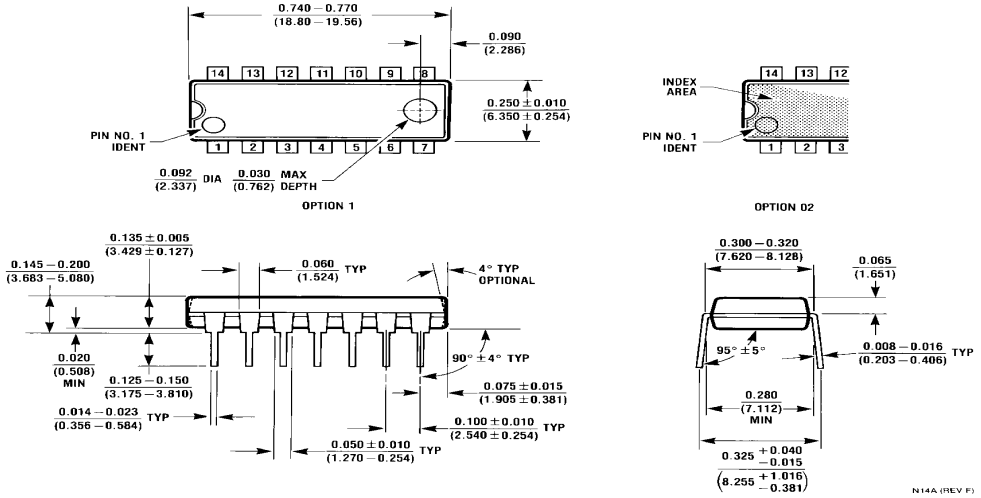
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC109 • 74ACT109
Dual JK Positive Edge-Triggered Flip-Flop

General Description

The AC/ACT109 consists of two high-speed completely independent transition clocked $J\overline{K}$ flip-flops. The clocking operation is independent of rise and fall times of the clock waveform. The $J\overline{K}$ design allows operation as a D-Type flip-flop (refer to AC/ACT74 data sheet) by connecting the J and $\overline{K}$ inputs together.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

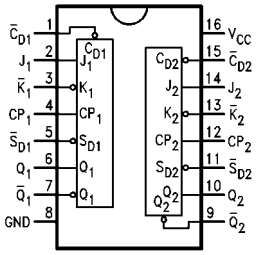
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- ACT109 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC109SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC109SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ Type II 5.3mm Wide
74AC109PC	N16E	16-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT109SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT109PC	N16E	16-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

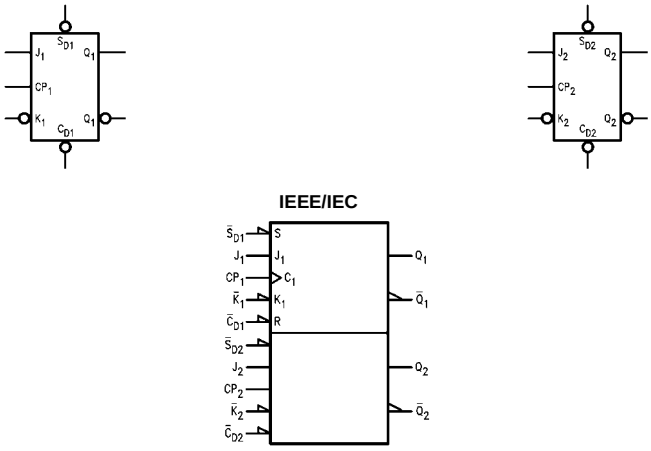


Pin Descriptions

Pin Names	Description
J_1, J_2, $\overline{K}_1$, $\overline{K}_2$	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Logic Symbols



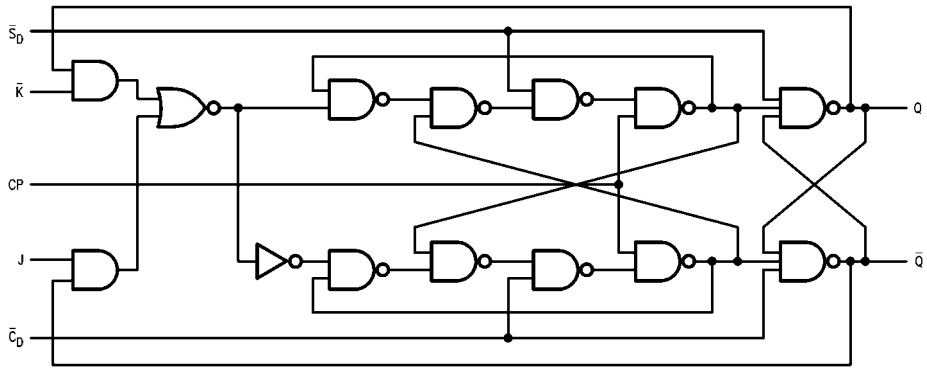
Truth Table

(each half)

Inputs					Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	J	$\overline{K}$	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	L	L	L	H
H	H	⌐	H	L	Toggle	
H	H	⌐	L	H	Q_0	$\overline{Q}_0$
H	H	⌐	H	H	H	L
H	H	L	X	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
⌐ = LOW-to-HIGH Transition
X = Immaterial
$Q_0(\overline{Q}_0)$ = Previous $Q_0(\overline{Q}_0)$ before LOW-to-HIGH Transition of Clock

Logic Diagram (one half shown)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables.Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	$FV_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	µA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	3.3	125	150		100		MHz
		5.0	150	175		125		
t_{PLH}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	3.3	4.0	8.0	13.5	3.5	16.0	ns
		5.0	2.5	6.0	10.0	2.0	10.5	
t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	3.3	3.0	8.0	14.0	3.0	14.5	ns
		5.0	2.0	6.0	10.0	1.5	10.5	
t_{PLH}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.3	3.0	8.0	12.0	2.5	13.0	ns
		5.0	2.5	6.0	9.0	2.0	10.0	
t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.3	3.0	10.0	12.0	3.0	13.5	ns
		5.0	2.0	7.5	9.5	2.0	10.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW J_n or $\overline{K}_n$ to CP_n	3.3 5.0	3.5 2.0	6.5 4.5	7.5 5.0	ns
t_H	Hold Time, HIGH or LOW J_n or $\overline{K}_n$ to CP_n	3.3 5.0	–1.5 –0.5	0 0.5	0 0.5	ns
t_W	Pulse Width $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$	3.3 5.0	2.0 2.0	7.0 4.5	7.5 5.0	ns
t_{REC}	Recovery Time $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP_n	3.3 5.0	–2.5 –1.5	0 0	0 0	ns

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	145	210		125		MHz
t_{PLH}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	5.0	4.0	7.0	11.0	3.5	13.0	ns
t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	5.0	3.0	6.0	10.0	2.5	11.5	ns
t_{PLH}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	5.0	2.5	6.0	10.0	2.0	11.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

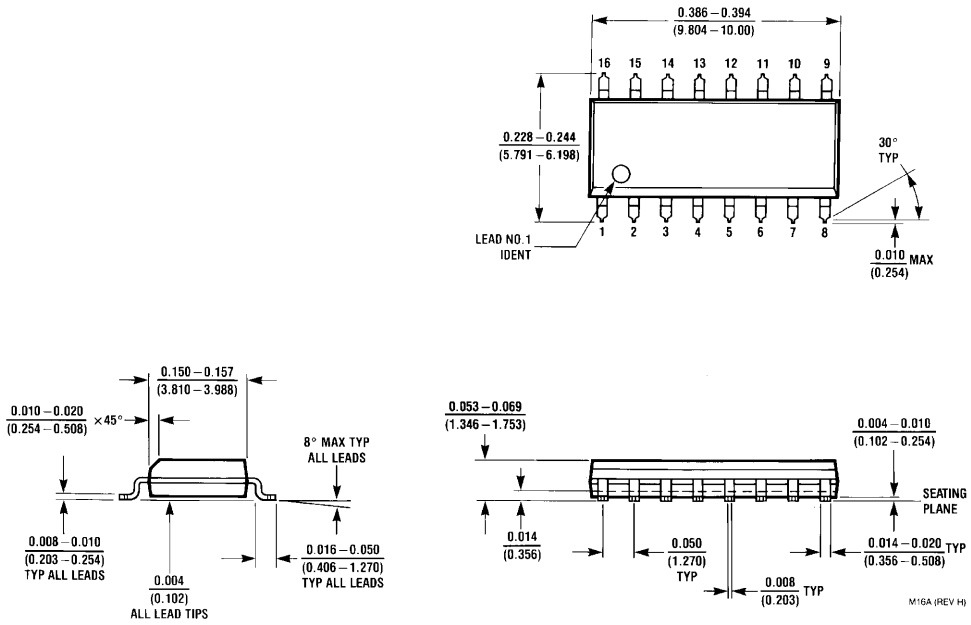
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW J_n or $\overline{K}_n$ to CP_n	5.0	0.5	2.0	2.5	ns
t_H	Hold Time, HIGH or LOW J_n or $\overline{K}_n$ to CP_n	5.0	0	2.0	2.0	ns
t_W	Pulse Width CP_n or $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$	5.0	3.0	5.0	6.0	ns
t_{rec}	Recovery Time $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP_n	5.0	–2.5	0	0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

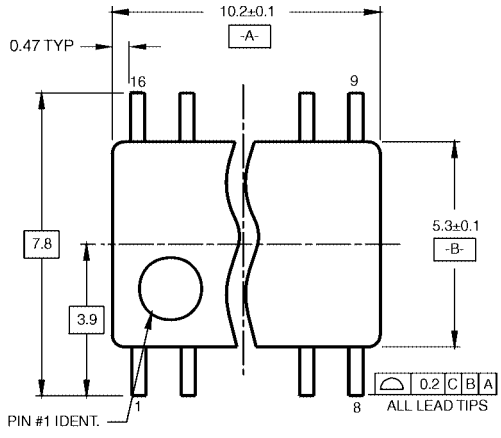
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	35.0	pF	V_{CC} = 5.0V

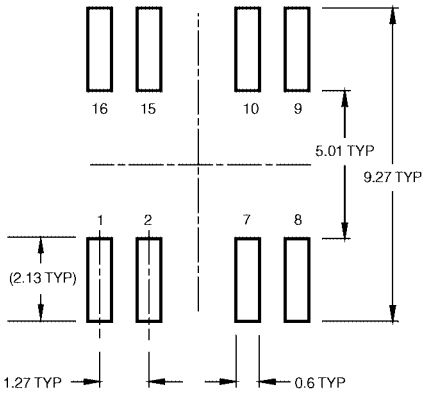
Physical Dimensions inches (millimeters) unless otherwise noted



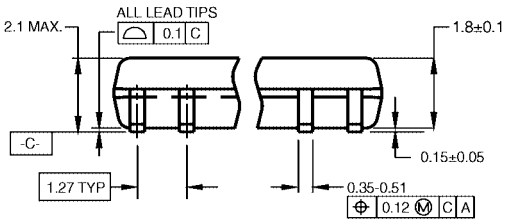
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

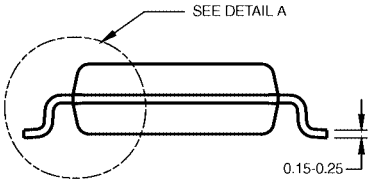
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



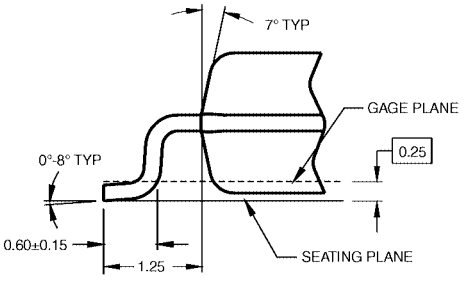


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

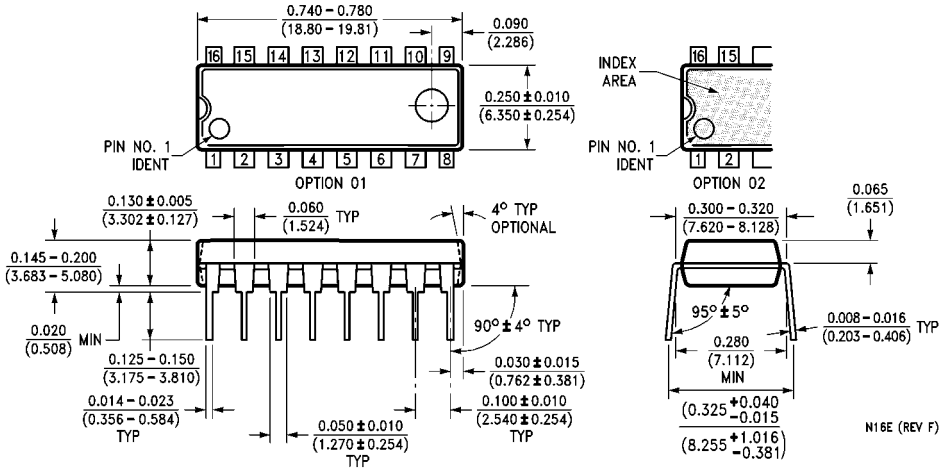
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC11
Triple 3-Input AND Gate

General Description

The AC11 contains three 3-input AND gates.

Features

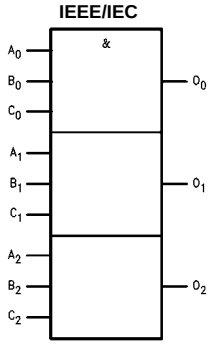
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA

Ordering Code:

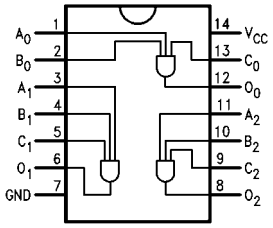
Order Number	Package Number	Package Description
74AC11SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74AC11MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC11PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n, C_n	Inputs
O_n	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	5.5	9.5	1.0	10.0	ns
		5.0	1.5	4.0	8.0	1.0	8.5	
t_{PHL}	Propagation Delay	3.3	1.5	5.5	8.5	1.0	9.5	ns
		5.0	1.5	4.0	7.0	1.0	7.5	

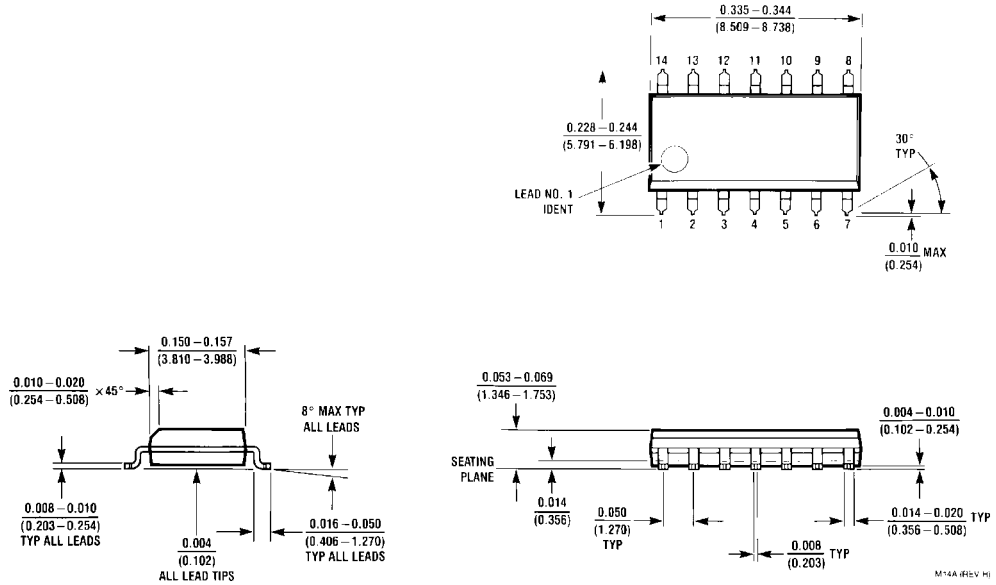
Note 5: Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

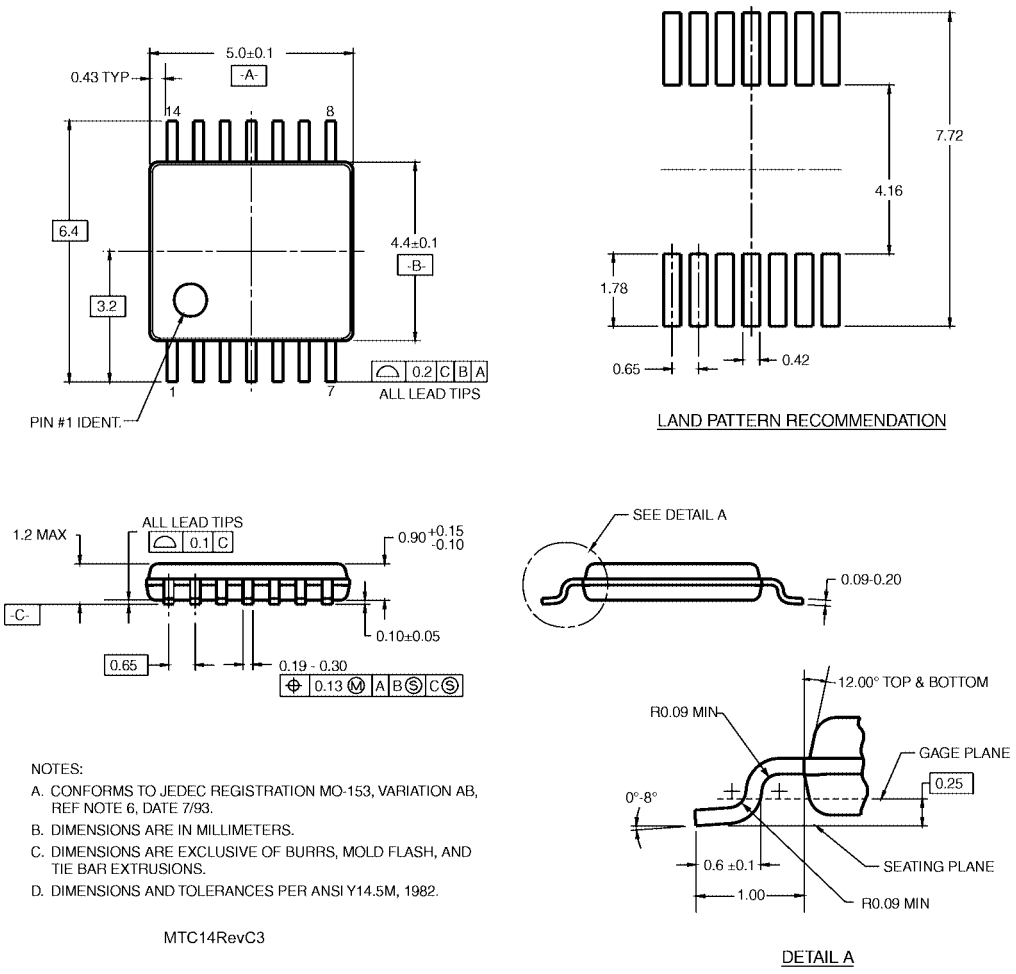
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	20.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

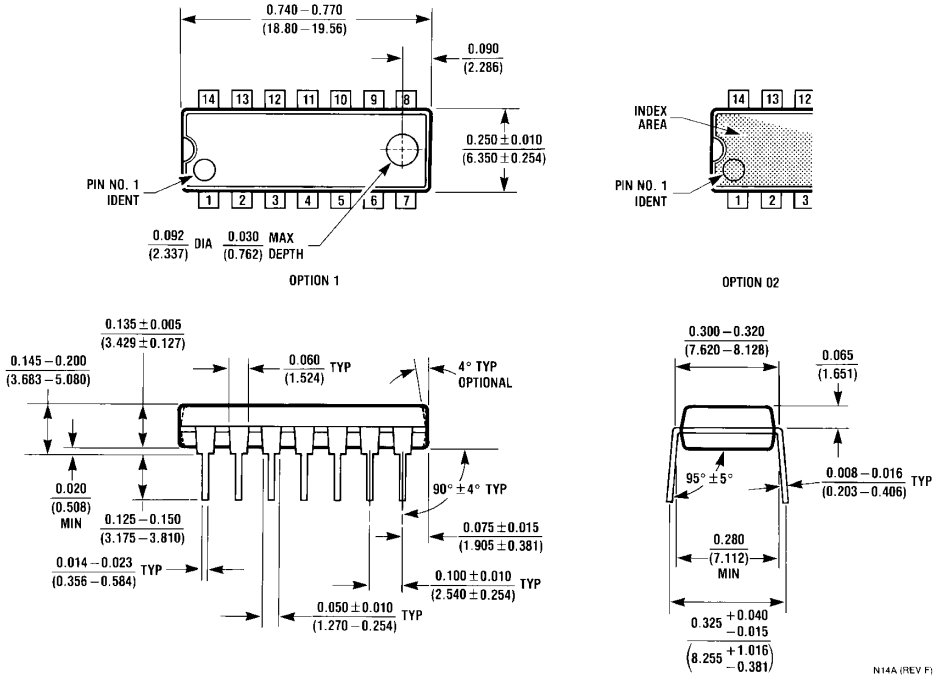
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

March 1990
Revised November 1999

74AC125 • 74ACT125
Quad Buffer with 3-STATE Outputs

General Description

The AC/ACT125 contains four independent non-inverting buffers with 3-STATE outputs.

Features

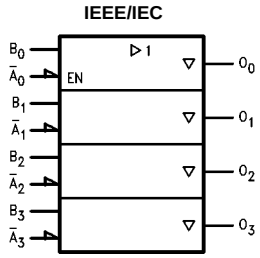
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- ACT125 has TTL-compatible outputs

Ordering Code:

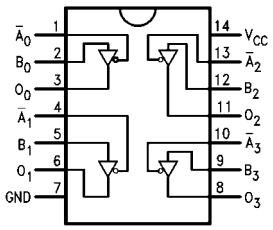
Order Number	Package Number	Package Description
74AC125SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC125PC	N14A	14-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT125SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT125PC	N14A	14-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{A}_n$, B_n	Inputs
O_n	Outputs

Function Table

Inputs		Output
A_n	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_K)	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices V_{IN} from 30% to 70% of V_{CC} V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices V_{IN} from 0.8V to 2.0V V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} =24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		± 0.25	± 2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, V_{GND} V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Note: I_{IN} and I_{CC}@ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
						V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76		$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
						V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44		$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$ (Note 7)
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

Note 7: May be measured per the JEDEC Alternate Method.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	3.3	1.0	6.5	9.0	1.0	10.0	ns
		5.0	1.0	5.5	7.0	1.0	7.5	
t_{PHL}	Propagation Delay Data to Output	3.3	1.0	6.5	9.0	1.0	10.0	ns
		5.0	1.0	5.0	7.0	1.0	7.5	
t_{PZH}	Output Enable Time	3.3	1.0	6.0	10.5	1.0	11.0	ns
		5.0	1.0	5.0	7.0	1.0	8.0	
t_{PZL}	Output Enable Time	3.3	1.0	7.5	10.0	1.0	11.0	ns
		5.0	1.0	5.5	8.0	1.0	8.5	
t_{PHZ}	Output Disable Time	3.3	1.0	7.5	10.0	1.0	10.5	ns
		5.0	1.0	6.5	9.0	1.0	9.5	
t_{PLZ}	Output Disable Time	3.3	1.0	7.5	10.5	1.0	11.5	ns
		5.0	1.0	6.5	9.0	1.0	9.5	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

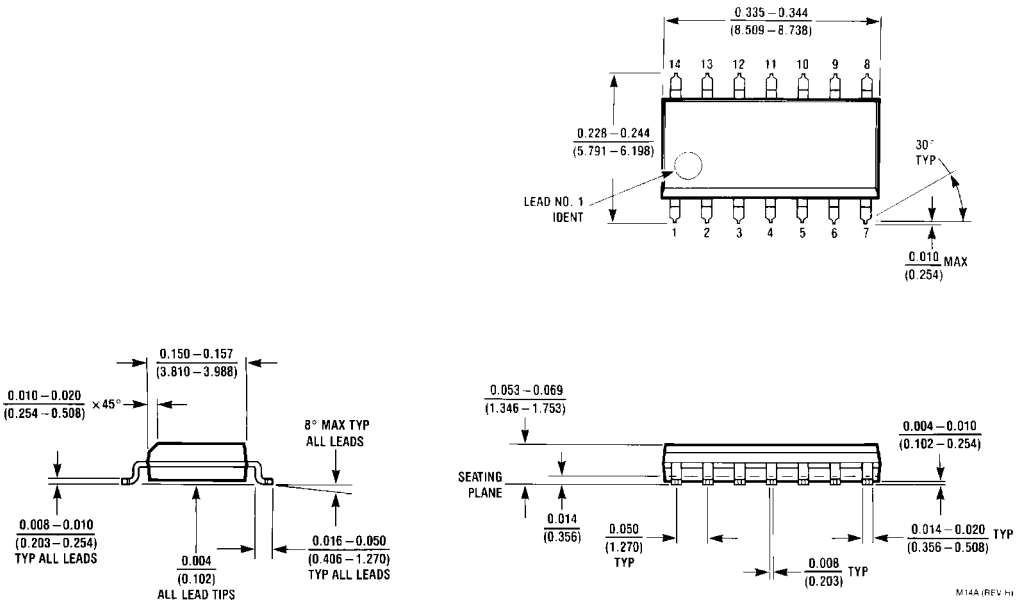
Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	1.0	6.5	9.0	1.0	10.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	1.0	7.0	9.0	1.0	10.0	ns
t_{PZH}	Output Enable Time	5.0	1.0	6.0	8.5	1.0	9.5	ns
t_{PZL}	Output Enable Time	5.0	1.0	7.0	9.5	1.0	10.5	ns
t_{PHZ}	Output Disable Time	5.0	1.0	7.0	9.5	1.0	10.5	ns
t_{PLZ}	Output Disable Time	5.0	1.0	7.5	10.0	1.0	10.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

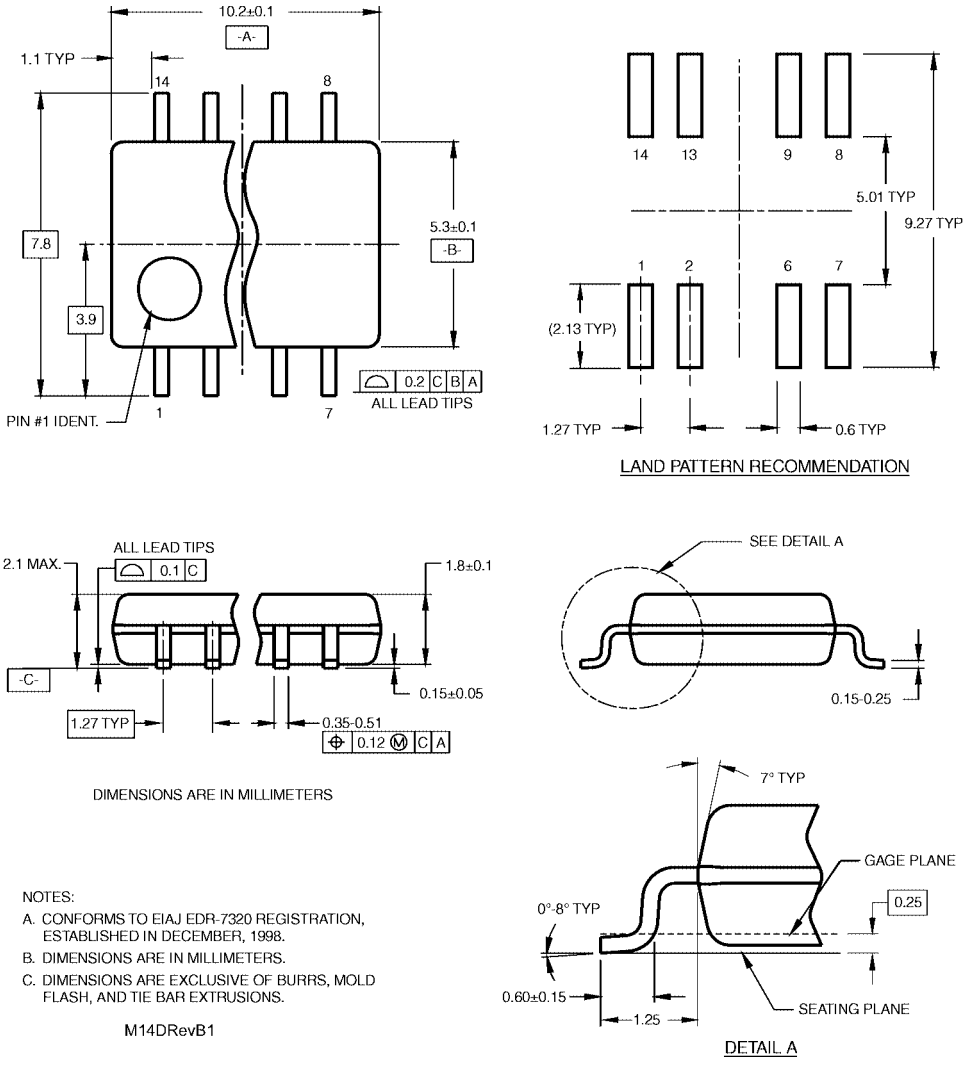
Symbol	Parameter	AC/ACT Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

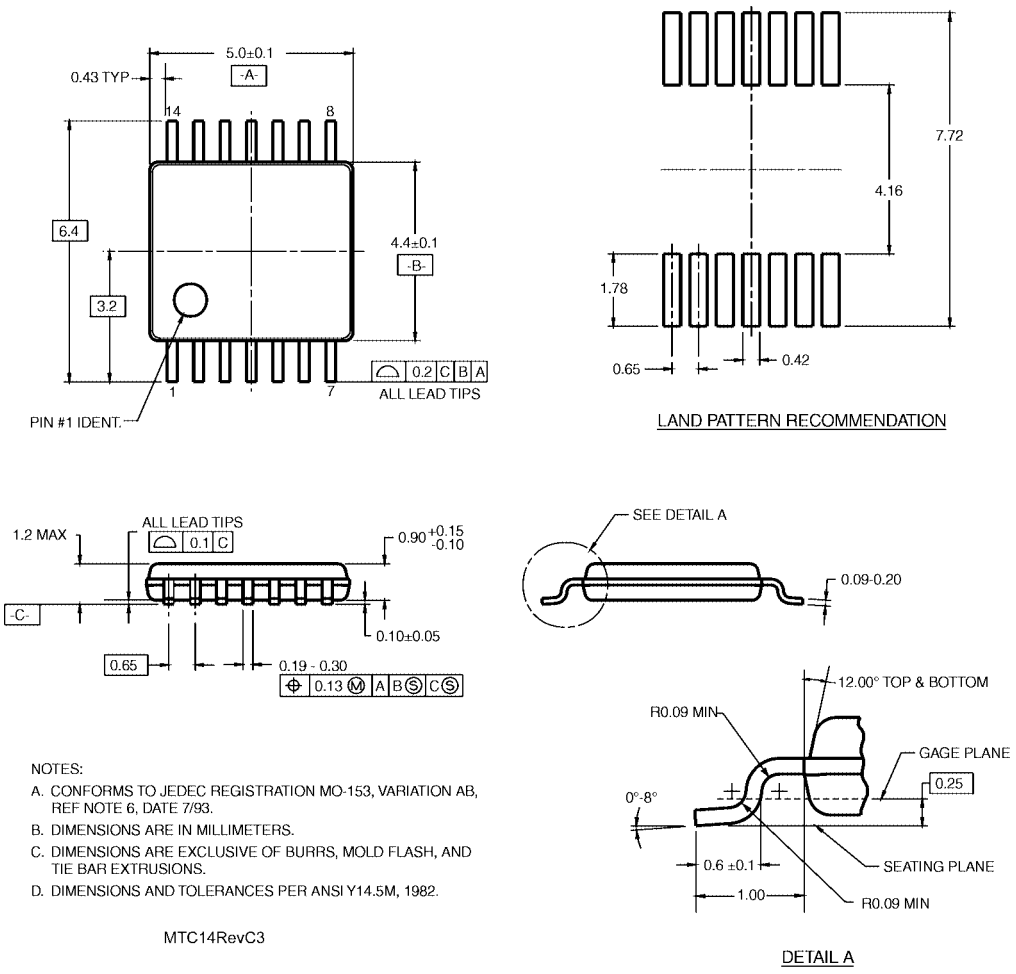
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

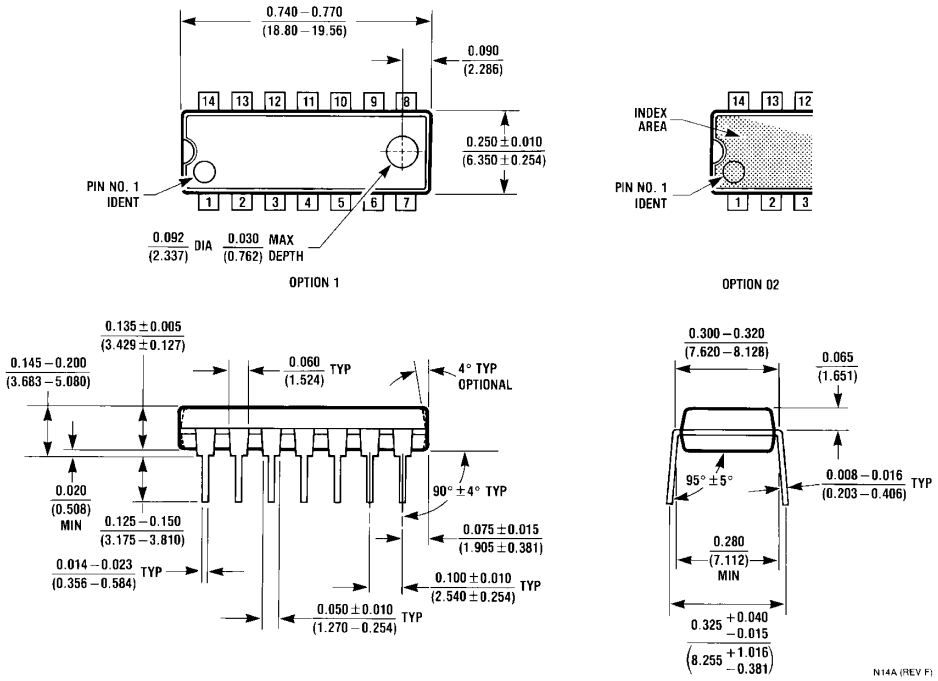
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC138 • 74ACT138
1-of-8 Decoder/Demultiplexer

General Description

The AC/ACT138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed bipolar memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three AC/ACT138 devices or a 1-of-32 decoder using four AC/ACT138 devices and one inverter.

Features

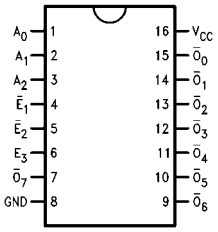
- I_{CC} reduced by 50%
- Demultiplexing capability
- Multiple input enable for easy expansion
- Active LOW mutually exclusive outputs
- Outputs source/sink 24 mA
- ACT138 has TTL-compatible inputs

Ordering Code:

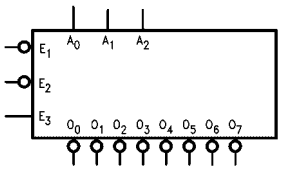
Order Number	Package Number	Package Description
74AC138SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74AC138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC138PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT138SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74ACT138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT138PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

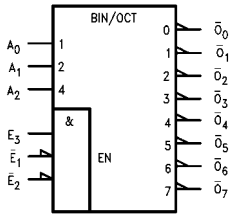
Connection Diagram



Logic Symbols



IEEE/IEC



Pin Descriptions

Pin Names	Description
A_0–A_2	Address Inputs
$\overline{E}_1$–$\overline{E}_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0$–$\overline{O}_7$	Outputs

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Truth Table

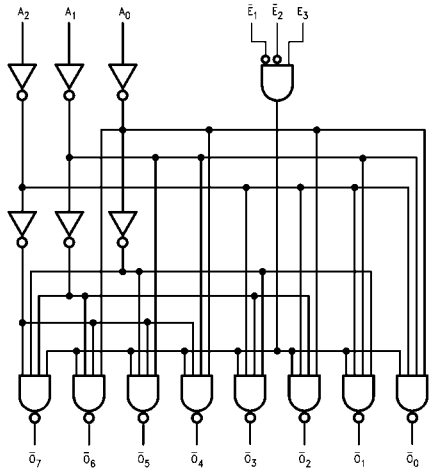
Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Functional Description

The AC/ACT138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A_0, A_1, A_2) and, when enabled, provides eight mutually exclusive active-LOW outputs ($\overline{O}_0$–$\overline{O}_7$). The AC/ACT138 features three Enable inputs, two active-LOW ($\overline{E}_1$, $\overline{E}_2$) and one active-HIGH (E_3). All outputs will be HIGH unless $\overline{E}_1$ and $\overline{E}_2$ are LOW and E_3 is HIGH. This multiple enable function allows easy parallel expansion of the device to a 1-of-32 (5 lines to 32 lines) decoder with just four AC/ACT138 devices and one inverter (see Figure 1). The AC/ACT138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active-HIGH or active-LOW state.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

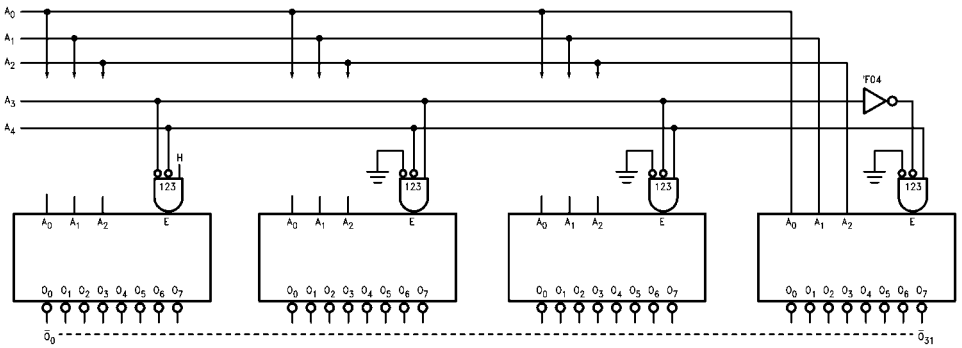


FIGURE 1. Expansion to 1-of-32 Decoding

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 24 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA 0
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL} 24 mA
		5.5		0.36	0.44		I_{OL}.= 24 mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay A_n to $\overline{O}_n$	3.3	1.5	8.5	13.0	1.5	15.0	ns
		5.0	1.5	6.5	9.5	1.5	10.5	
t_{PHL}	Propagation Delay A_n to $\overline{O}_n$	3.3	1.5	8.0	12.5	1.5	14.0	ns
		5.0	1.5	6.0	9.0	1.5	10.5	
t_{PLH}	Propagation Delay $\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	3.3	1.5	11.0	15.0	1.5	16.0	ns
		5.0	1.5	8.0	11.0	1.5	12.0	
t_{PHL}	Propagation Delay $\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	3.3	1.5	9.5	13.5	1.5	15.0	ns
		5.0	1.5	7.0	9.5	1.5	10.5	
t_{PLH}	Propagation Delay E_3 to $\overline{O}_n$	3.3	1.5	11.0	15.5	1.5	16.5	ns
		5.0	1.5	8.0	11.0	1.5	12.5	
t_{PHL}	Propagation Delay E_3 to $\overline{O}_n$	3.3	1.5	8.5	13.0	1.5	14.0	ns
		5.0	1.5	6.0	8.0	1.0	9.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

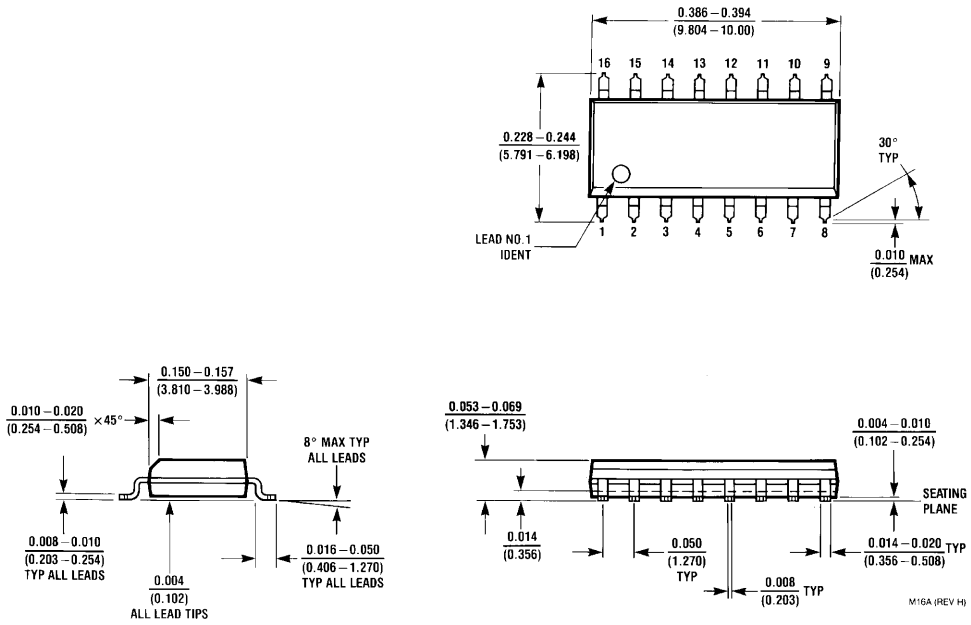
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay A_n to $\overline{O}_n$	5.0	1.5	7.0	10.5	1.5	11.5	ns
t_{PHL}	Propagation Delay A_n to $\overline{O}_n$	5.0	1.5	6.5	10.5	1.5	11.5	ns
t_{PLH}	Propagation Delay $\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	5.0	2.5	8.0	11.5	2.0	12.5	ns
t_{PHL}	Propagation Delay $\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	5.0	2.0	7.5	11.5	2.0	12.5	ns
t_{PLH}	Propagation Delay E_3 to $\overline{O}n$	5.0	2.5	8.0	12.0	2.0	13.0	ns
t_{PHL}	Propagation Delay E_3 to $\overline{O}n$	5.0	2.0	6.5	10.5	1.5	11.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

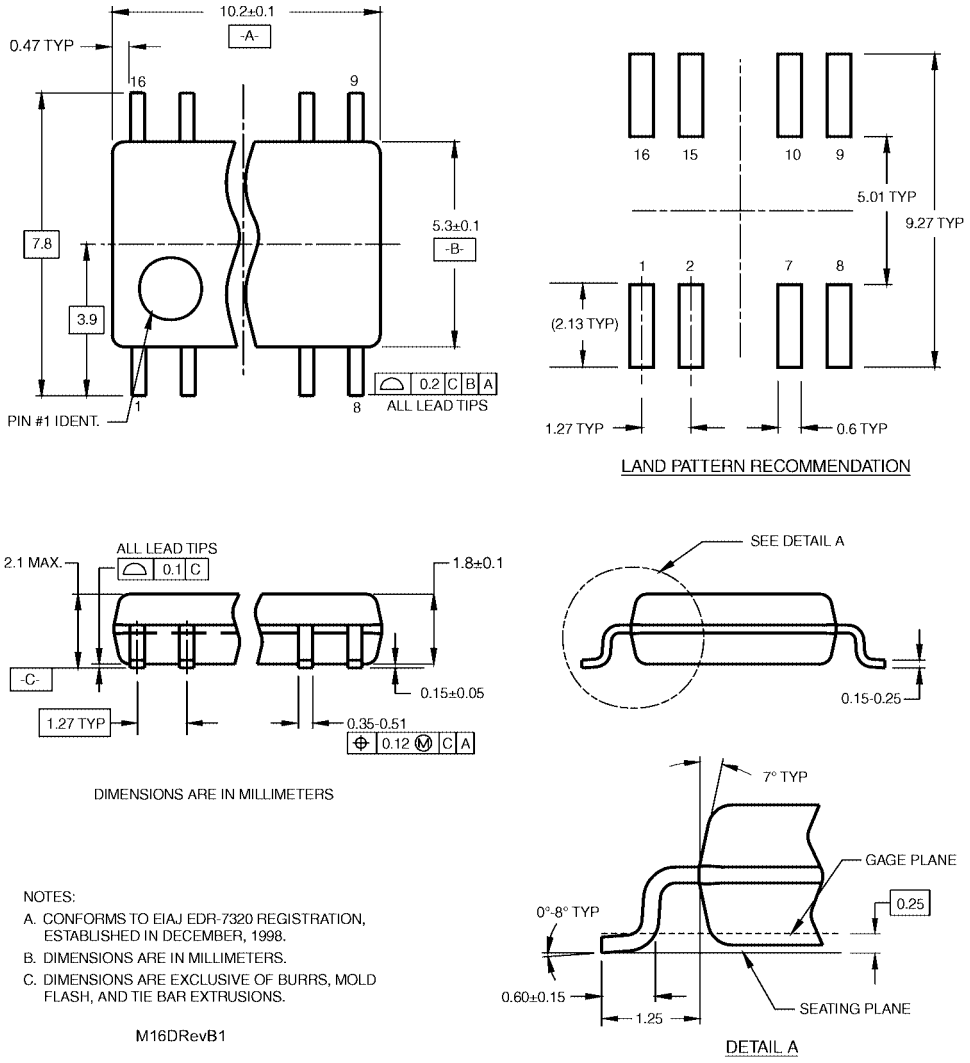
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	60.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

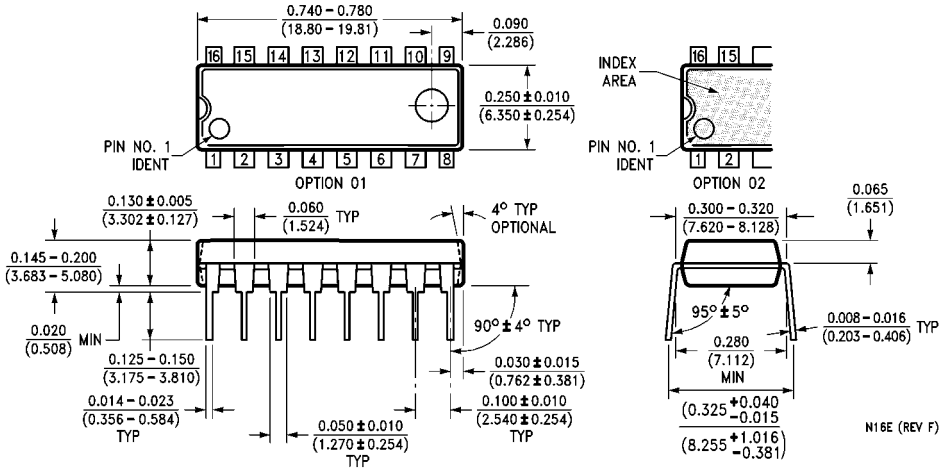
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

16-Lead Small Outline Package (SOP), EIAJ Type II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC139 • 74ACT139
Dual 1-of-4 Decoder/Demultiplexer

General Description

The AC/ACT139 is a high-speed, dual 1-of-4 decoder/demultiplexer. The device has two independent decoders, each accepting two inputs and providing four mutually-exclusive active-LOW outputs. Each decoder has an active-LOW Enable input which can be used as a data input for a 4-output demultiplexer. Each half of the AC/ACT139 can be used as a function generator providing all four minterms of two variables.

Features

- I_{CC} reduced by 50%
- Multifunction capability
- Two completely independent 1-of-4 decoders
- Active LOW mutually exclusive outputs
- Outputs source/sink 24 mA
- ACT139 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC139SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC139SJ	M16D	16-Lead Small Outline Package (SOIC), EIAJ Type II, 5.3mm Wide
74AC139MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC139PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT139SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT139SJ	M16D	16-Lead Small Outline Package (SOIC), EIAJ Type II, 5.3mm Wide
74ACT139MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
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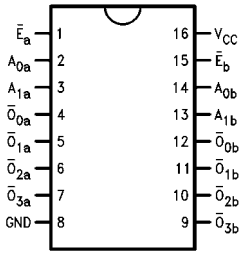
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

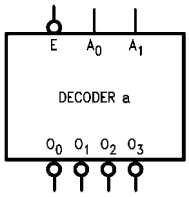


Pin Descriptions

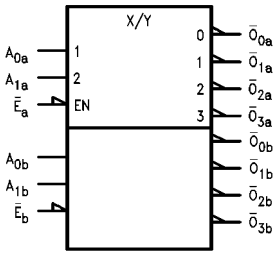
Pin Names	Description
A_0, A_1	Address Inputs
$\overline{E}$	Enable Inputs
$\overline{O}_0$–$\overline{O}_3$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC



Functional Description

The AC/ACT139 is a high-speed dual 1-of-4 decoder/demultiplexer. The device has two independent decoders, each of which accepts two binary weighted inputs (A_0–A_1) and provides four mutually exclusive active-LOW outputs ($\overline{O}_0$–$\overline{O}_3$). Each decoder has an active-LOW enable ($\overline{E}$). When $\overline{E}$ is HIGH all outputs are forced HIGH. The enable can be used as the data input for a 4-output demultiplexer application. Each half of the AC/ACT139 generates all four minterms of two variables. These four minterms are useful in some applications, replacing multiple gate functions as shown in Figure 1, and thereby reducing the number of packages required in a logic network.

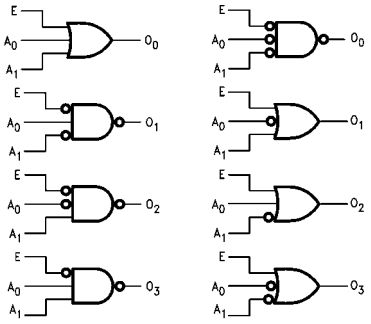


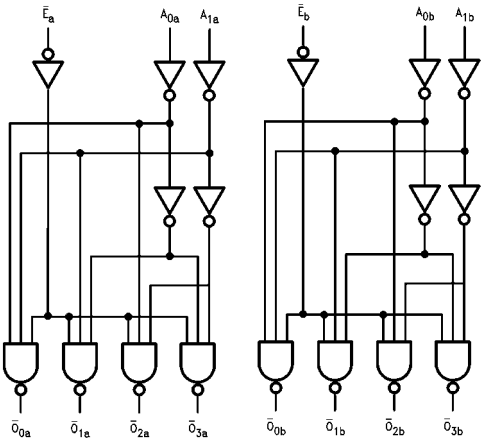
FIGURE 1. Gate Functions (Each Half)

Truth Table

Inputs			Outputs			
$\overline{E}$	A_0	A_1	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	H	L	H	L	H	H
L	L	H	H	H	L	H
L	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay A_n to $\overline{O}_n$	3.3	4.0	8.0	11.5	3.5	13.0	ns
		5.0	3.0	6.5	8.5	2.5	9.5	
t_{PHL}	Propagation Delay A_n to $\overline{O}_n$	3.3	3.0	7.0	10.0	2.5	11.0	ns
		5.0	2.5	5.5	7.5	2.0	8.5	
t_{PLH}	Propagation Delay $\overline{E}_n$ to $\overline{O}_n$	3.3	4.5	9.5	12.0	3.5	13.0	ns
		5.0	3.5	7.0	8.5	3.0	10.0	
t_{PHL}	Propagation Delay $\overline{E}_n$ to $\overline{O}_n$	3.3	4.0	8.0	10.0	3.0	11.0	ns
		5.0	2.5	6.0	7.5	2.5	8.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V.
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

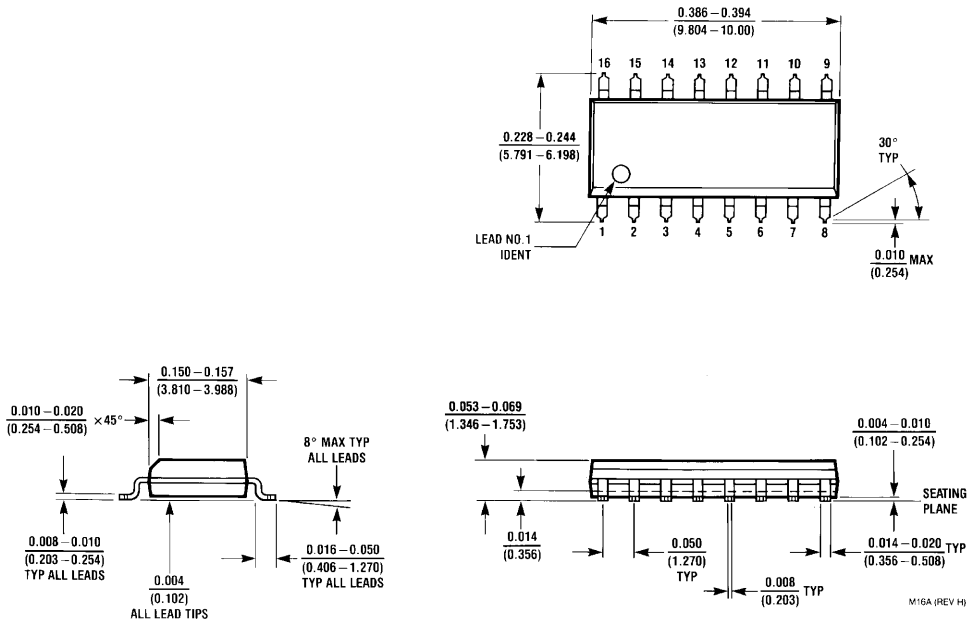
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay A_n to $\overline{O}_n$	5.0	1.5	6.0	8.5	1.5	9.5	ns
t_{PHL}	Propagation Delay A_n to $\overline{O}_n$	5.0	1.5	6.0	9.5	1.5	10.5	ns
t_{PLH}	Propagation Delay $\overline{E}_n$ to $\overline{O}_n$	5.0	2.5	7.0	10.0	2.0	11.0	ns
t_{PHL}	Propagation Delay $\overline{E}_n$ to $\overline{O}_n$	5.0	2.0	7.0	9.5	1.5	10.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

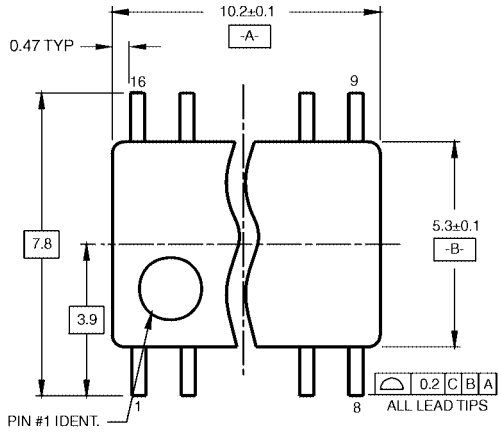
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

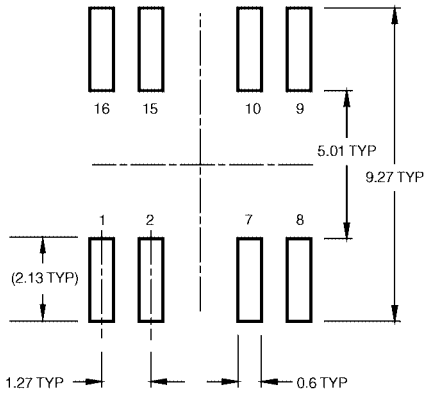
Physical Dimensions inches (millimeters) unless otherwise noted



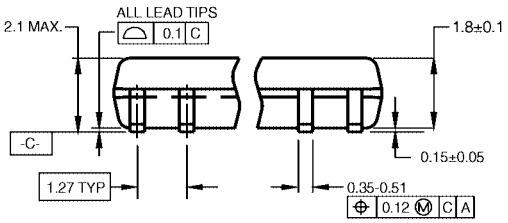
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION



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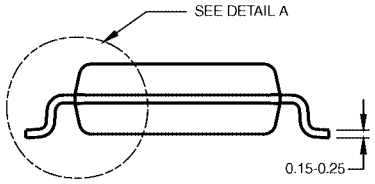
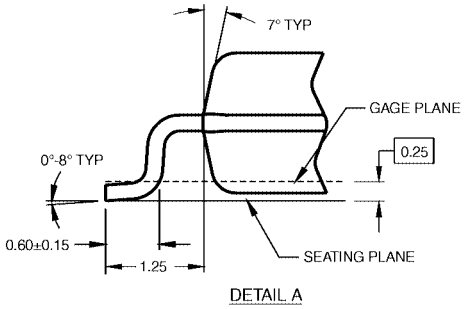




DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

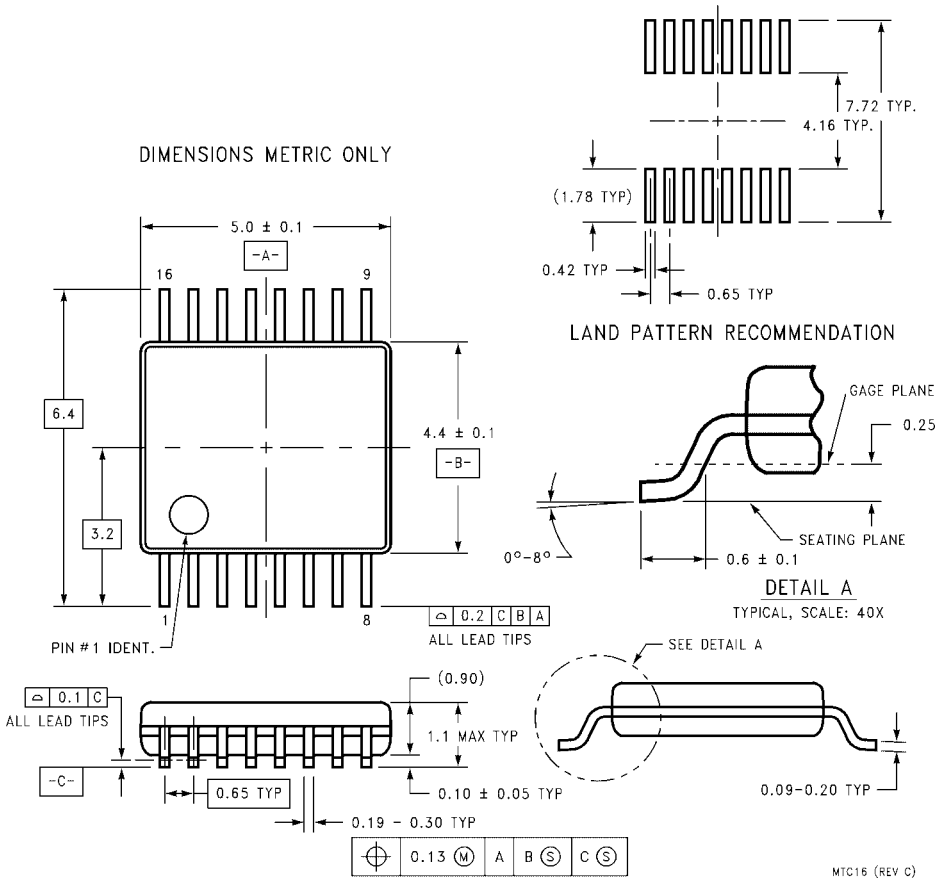
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

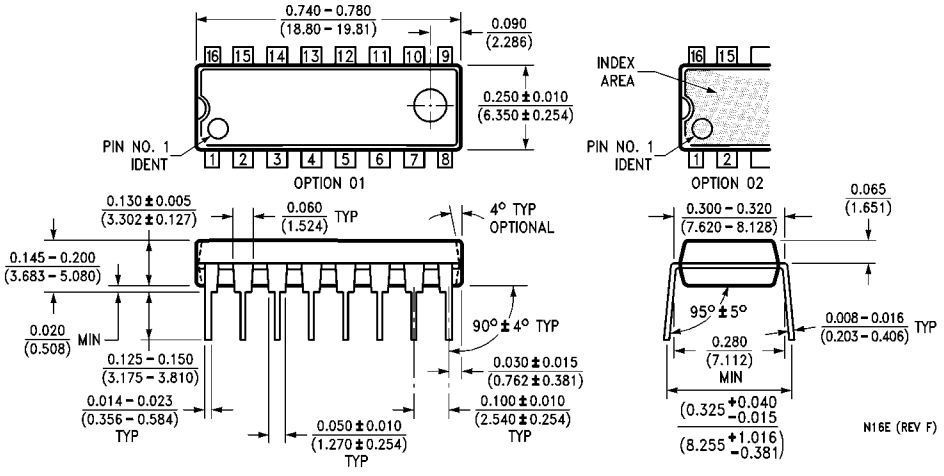
16-Lead Small Outline Package (SOP), EIAJ Type II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised December 1999

74AC14 • 74ACT14
Hex Inverter with Schmitt Trigger Input

General Description

The 74AC14 and 74ACT14 contain six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The 74AC14 and 74ACT14 have hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

Features

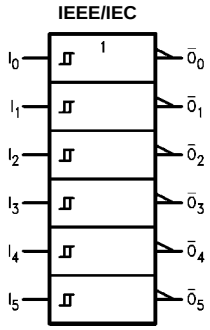
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- 74ACT14 has TTL-compatible inputs

Ordering Code:

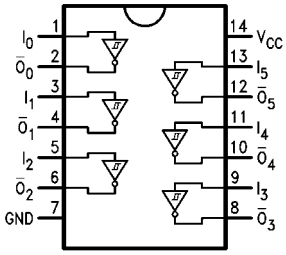
Order Number	Package Number	Package Description
74AC14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MS-153, 4.4mm Wide
74AC14PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MS-153, 4.4mm Wide
74ACT14PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
I_n	Inputs
$\overline{O}_n$	Outputs

Function Table

Input	Output
A	**$\overline{O}$**
L	H
H	L

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
		3.0		2.56	2.46	V	I_{OH} = 12
		4.5		3.86	3.76		I_{OH} = 24 mA
		5.5		4.86	4.76		I_{OH} = 24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
		3.0		0.36	0.44	V	I_{OL} = 12
		4.5		0.36	0.44		I_{OL} 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
V_{t+}	Maximum Positive Threshold	3.0		2.2	2.2	V	T_A = Worst Case
		4.5		3.2	3.2		
		5.5		3.9	3.9		
V_{t-}	Minimum Negative Threshold	3.0		0.5	0.5	V	T_A = Worst Case
		4.5		0.9	0.9		
		5.5		1.1	1.1		
$V_{H(MAX)}$	Maximum Hysteresis	3.0		1.2	1.2	V	T_A = Worst Case
		4.5		1.4	1.4		
		5.5		1.6	1.6		
$V_{H(MIN)}$	Minimum Hysteresis	3.0		0.3	0.3	V	T_A = Worst Case
		4.5		0.4	0.4		
		5.5		0.5	0.5		
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	µA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	9.5	13.5	1.5	15.0	ns
		5.0	1.5	7.0	10.0	1.5	11.0	
t_{PHL}	Propagation Delay	3.3	1.5	7.5	11.5	1.5	13.0	ns
		5.0	1.5	6.0	8.5	1.5	9.5	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	2.0	2.0		or $V_{CC} - 0.1V$
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$
	Output Voltage	5.5	1.5	0.8	0.8		or $V_{CC} - 0.1V$
V_{OH}	Minimum HIGH Level	4.5	4.49	434	4.4	V	$I_{OUT} = -50\mu A$
	Output Voltage	5.5	5.49	5.4	5.4		
						V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76		$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 6)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
	Output Voltage	5.5	0.001	0.1	0.1		
						V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44		$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 6)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
$V_{H(MAX)}$	Maximum Hysteresis	4.5		1.4	1.4	V	T_A = Worst Case
		5.5		1.6	1.6		
$V_{H(MIN)}$	Minimum Hysteresis	4.5		0.4	0.4	V	T_A = Worst Case
		5.5		0.5	0.5		
V_{t+}	Maximum Positive	4.5		2.0	2.0	V	T_A = Worst Case
	Threshold	5.5		2.0	2.0		
V_{t-}	Minimum Negative	4.5		0.8	0.8	V	T_A = Worst Case
	Threshold	5.5		0.8	0.8		
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 7)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent	5.5		2.0	20.0	µA	$V_{IN} = V_{CC}$
	Supply Current						or GND

Note 6: All outputs loaded; thresholds on input associated with output under test.

Note 7: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for ACT

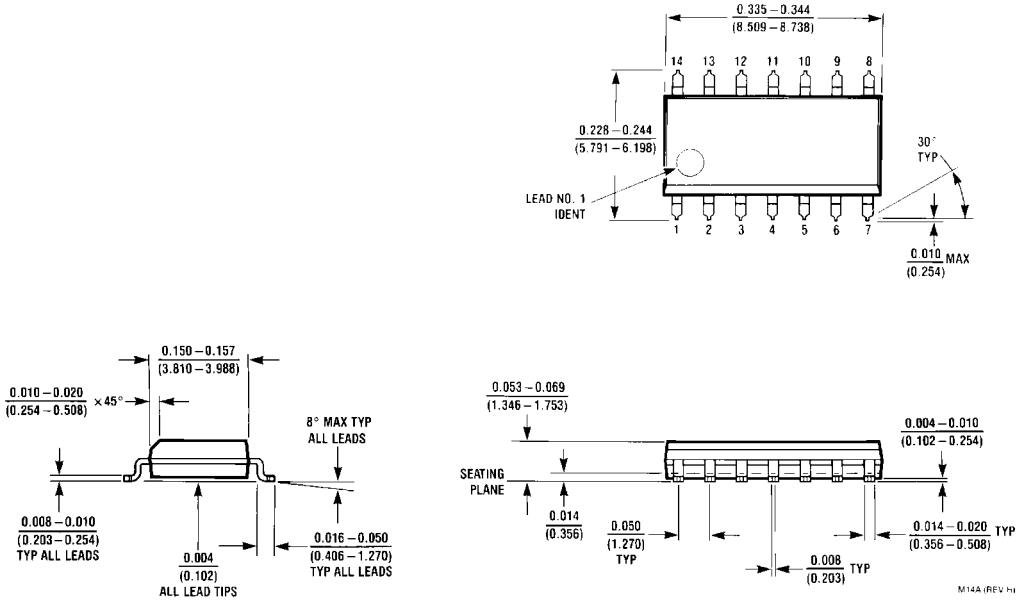
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	3.0	8.0	10.0	3.0	11.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	3.0	8.0	10.0	3.0	11.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

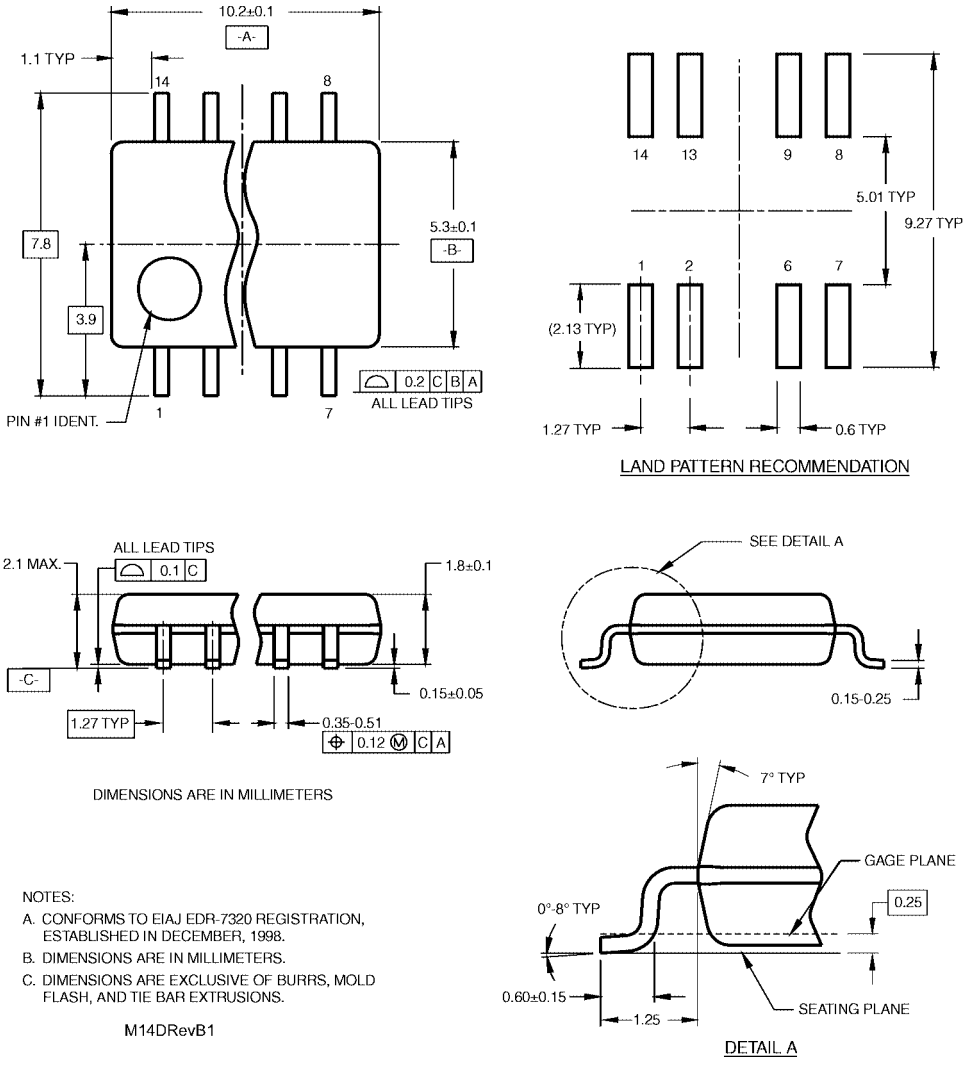
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance for AC for ACT	25.0 80	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

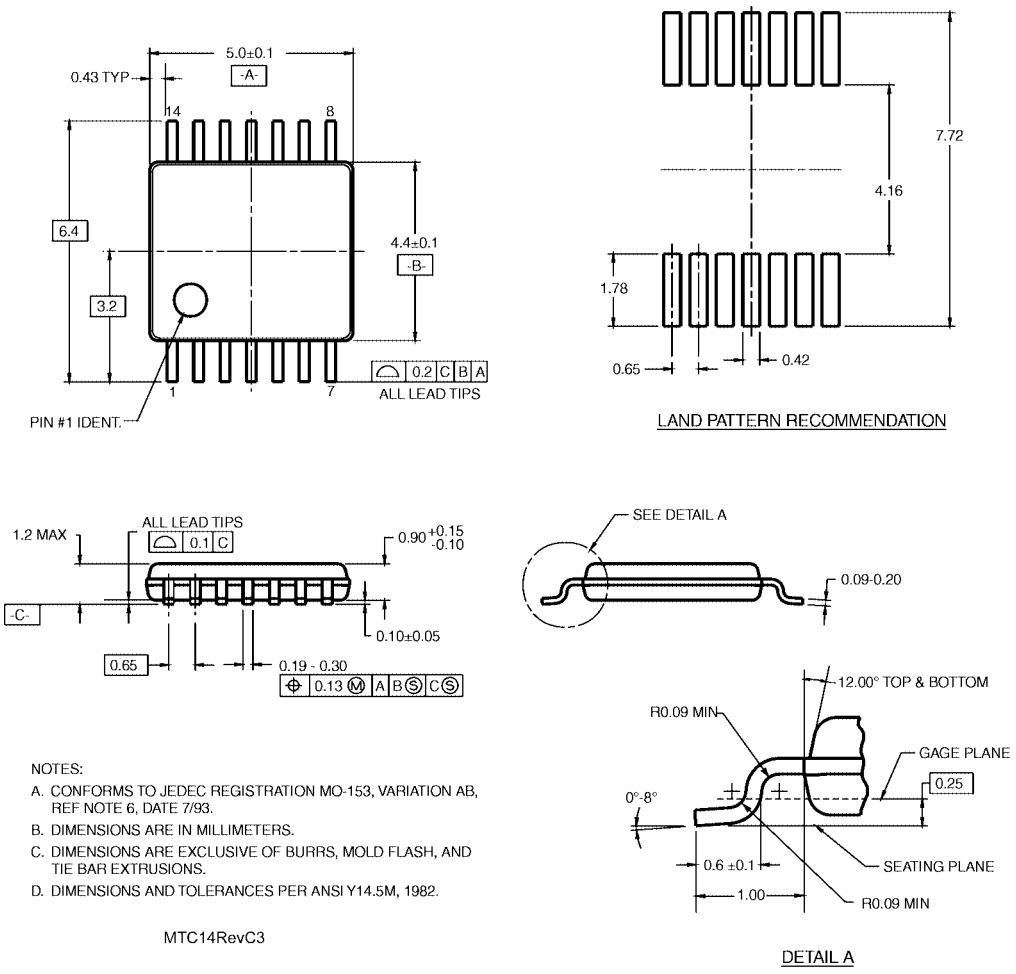
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

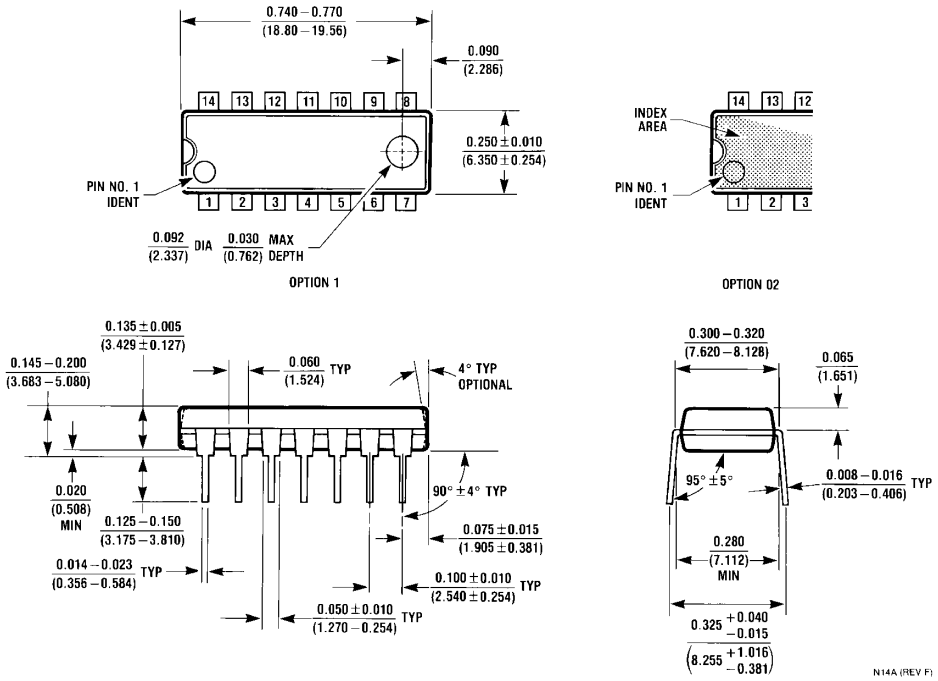
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC151 • 74ACT151
8-Input Multiplexer

General Description

The AC/ACT151 is a high-speed 8-input digital multiplexer. It provides, in one package, the ability to select one line of data from up to eight sources. The AC/ACT151 can be used as a universal function generator to generate any logic function of four variables. Both true and complementary outputs are provided.

Features

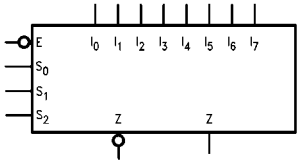
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- ACT151 has TTL-compatible inputs

Ordering Code:

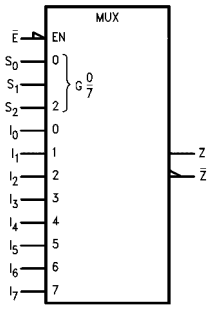
Order Number	Package Number	Package Description
74AC151SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74AC151SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC151MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC151PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT151SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74ACT151SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT151PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

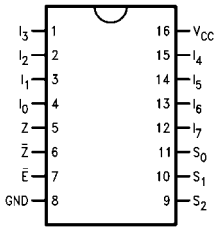
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_0–I_7	Data Inputs
S_0–S_2	Select Inputs
$\overline{E}$	Enable Input
Z	Data Output
$\overline{Z}$	Inverted Data Output

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Truth Table

Inputs				Outputs	
$\overline{E}$	S_2	S_1	S_0	$\overline{Z}$	Z
H	X	X	X	H	L
L	L	L	L	$\overline{I}_0$	I_0
L	L	L	H	$\overline{I}_1$	I_1
L	L	H	L	$\overline{I}_2$	I_2
L	L	H	H	$\overline{I}_3$	I_3
L	H	L	L	$\overline{I}_4$	I_4
L	H	L	H	$\overline{I}_5$	I_5
L	H	H	L	$\overline{I}_6$	I_6
L	H	H	H	$\overline{I}_7$	I_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

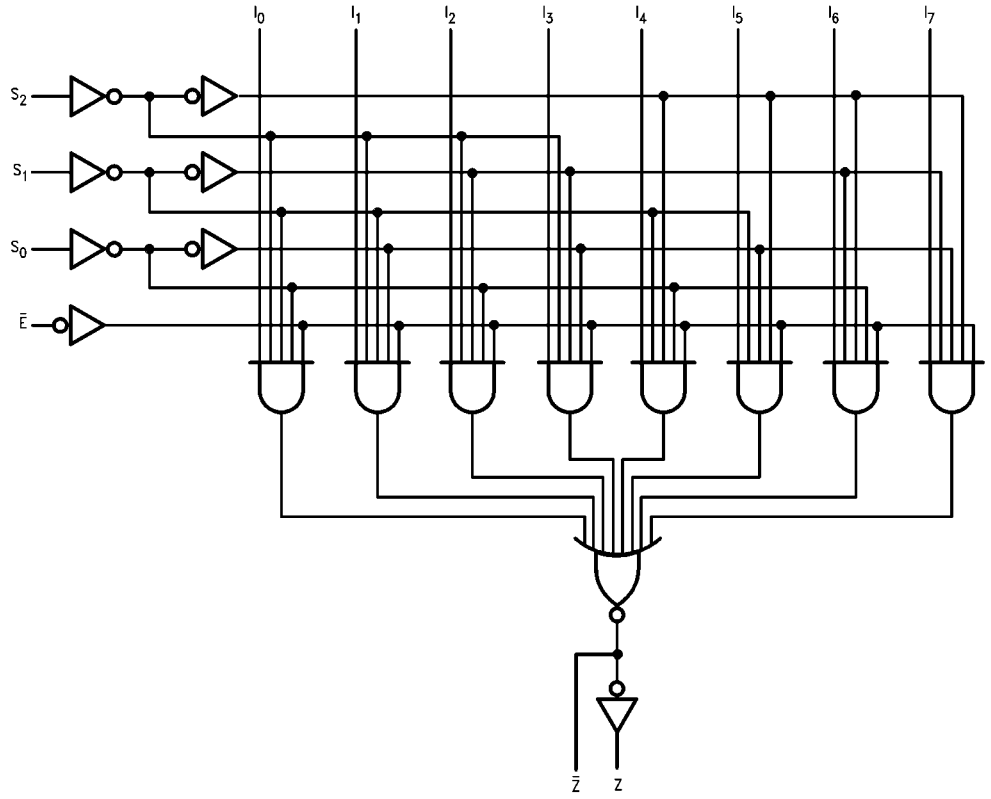
Functional Description

The AC/ACT151 is a logic implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0, S_1, S_2. Both true and complementary outputs are provided. The Enable input ($\overline{E}$) is active LOW. When it is not activated, the complementary output is HIGH and the true output is LOW regardless of all other inputs. The logic function provided at the output is:

$$Z = \overline{E} \bullet (I_0 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_1 \bullet S_0 \bullet \overline{S}_1 \bullet \overline{S}_2 +$$
$$I_2 \bullet \overline{S}_0 \bullet S_1 \bullet \overline{S}_2 + I_3 \bullet S_0 \bullet S_1 \bullet \overline{S}_2 + I_4 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet S_2 + I_5 \bullet$$
$$S_0 \bullet \overline{S}_1 \bullet S_2 + I_6 \bullet \overline{S}_0 \bullet S_1 \bullet S_2 + I_7 \bullet S_0 \bullet S_1 \bullet S_2)$$

The AC/ACT151 provides the ability, in one package, to select from eight sources of data or control information. By proper manipulation of the inputs, the AC/ACT151 can provide any logic function of four variables and its complement.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA(Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay S_n to Z or $\overline{Z}$	3.3	3.0	11.5	18.0	3.0	20.0	ns
		5.0	2.5	8.5	13.0	2.0	15.0	
t_{PHL}	Propagation Delay S_n to Z or $\overline{Z}$	3.3	2.5	12.0	18.0	2.5	20.0	ns
		5.0	2.0	8.5	13.0	1.5	15.0	
t_{PLH}	Propagation Delay $\overline{E}$ to Z or $\overline{Z}$	3.3	2.5	8.0	13.0	2.0	14.0	ns
		5.0	2.0	6.0	10.0	1.5	11.0	
t_{PHL}	Propagation Delay $\overline{E}$ to Z or $\overline{Z}$	3.3	1.5	8.5	13.0	1.5	14.0	ns
		5.0	1.5	6.5	10.0	1.5	11.0	
t_{PLH}	Propagation Delay I_n to Z or $\overline{Z}$	3.3	2.5	9.5	14.0	2.0	15.5	ns
		5.0	1.5	7.0	10.5	1.5	11.0	
t_{PHL}	Propagation Delay I_n to Z or $\overline{Z}$	3.3	2.5	9.5	15.0	2.0	16.0	ns
		5.0	1.5	7.0	11.0	1.5	12.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

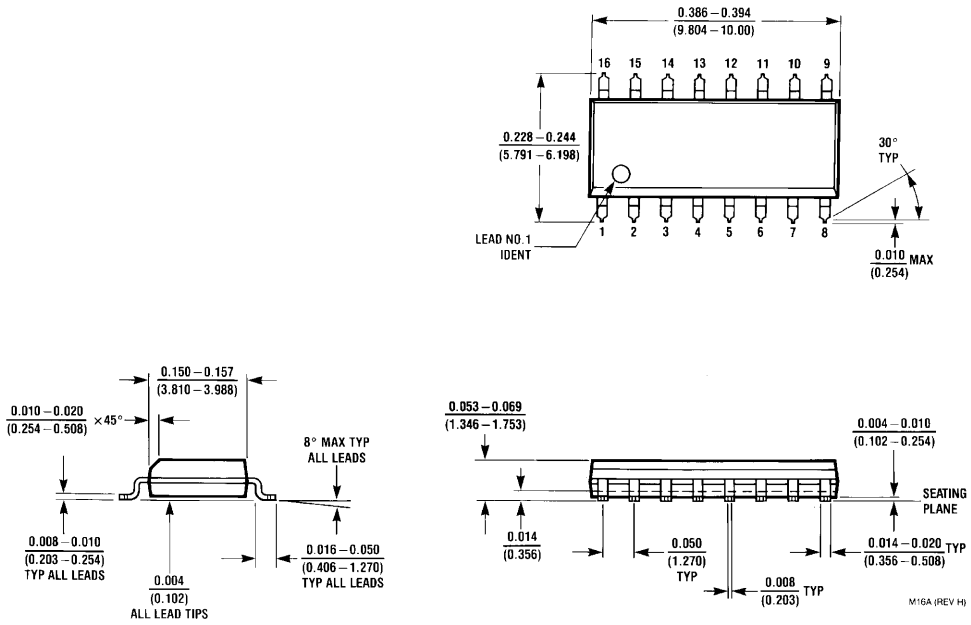
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z	5.0	3.5	12.5	15.5	3.0	17.0	ns
t_{PHL}	Propagation Delay S_n to Z	5.0	3.5	12.5	15.5	3.0	16.5	ns
t_{PLH}	Propagation Delay S_n to $\overline{Z}$	5.0	3.5	12.5	15.0	3.0	16.5	ns
t_{PHL}	Propagation Delay S_n to $\overline{Z}$	5.0	4.0	12.5	16.5	3.5	18.5	ns
t_{PLH}	Propagation Delay $\overline{E}$ to Z	5.0	2.5	6.0	9.5	2.5	10.0	ns
t_{PHL}	Propagation Delay $\overline{E}$ to Z	5.0	2.5	6.0	9.0	2.5	10.0	ns
t_{PLH}	Propagation Delay $\overline{E}$ to $\overline{Z}$	5.0	2.5	6.0	8.5	2.5	9.5	ns
t_{PHL}	Propagation Delay $\overline{E}$ to $\overline{Z}$	5.0	3.0	6.5	10.0	2.5	10.5	ns
t_{PLH}	Propagation Delay I_n to Z	5.0	3.5	7.5	11.5	3.0	12.5	ns
t_{PHL}	Propagation Delay I_n to Z	5.0	3.5	8.0	12.0	3.0	13.5	ns
t_{PLH}	Propagation Delay I_n to $\overline{Z}$	5.0	3.5	8.0	12.0	3.0	13.0	ns
t_{PHL}	Propagation Delay I_n to $\overline{Z}$	5.0	4.0	8.0	12.5	3.0	14.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

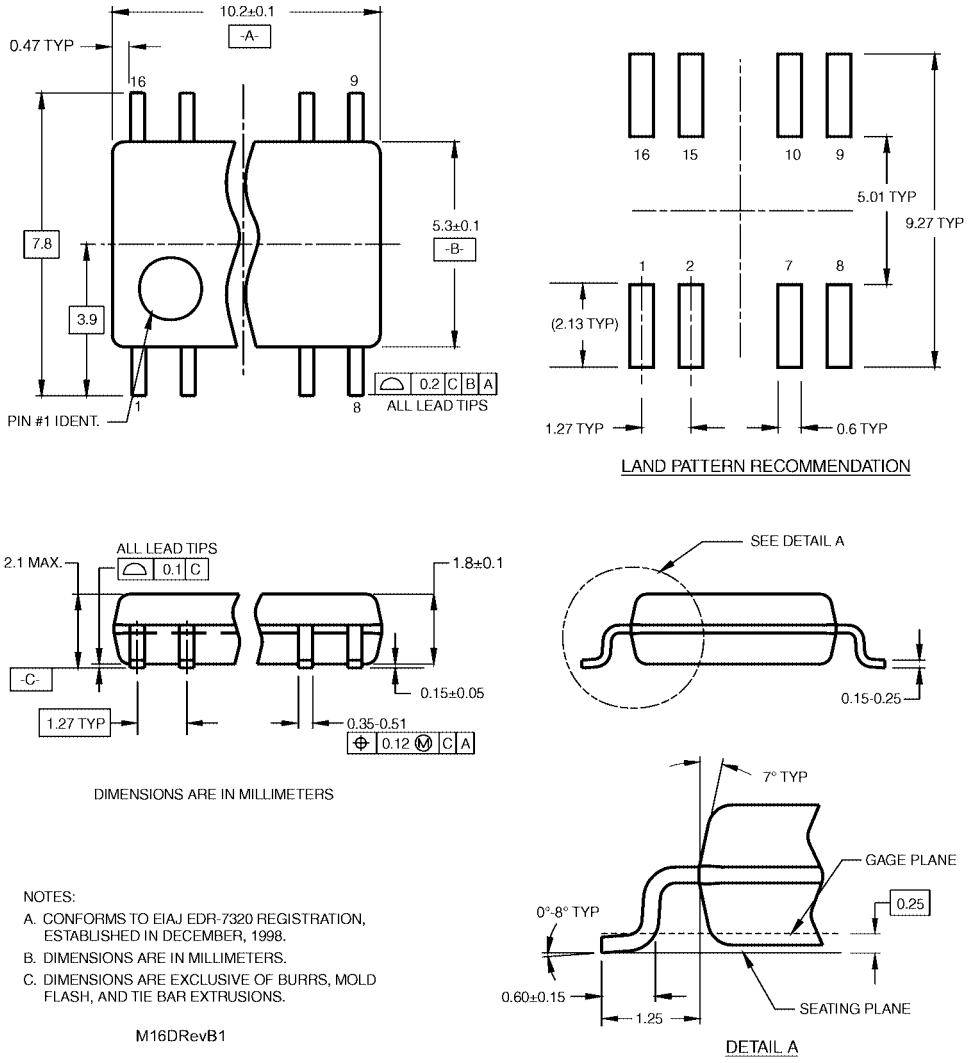
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

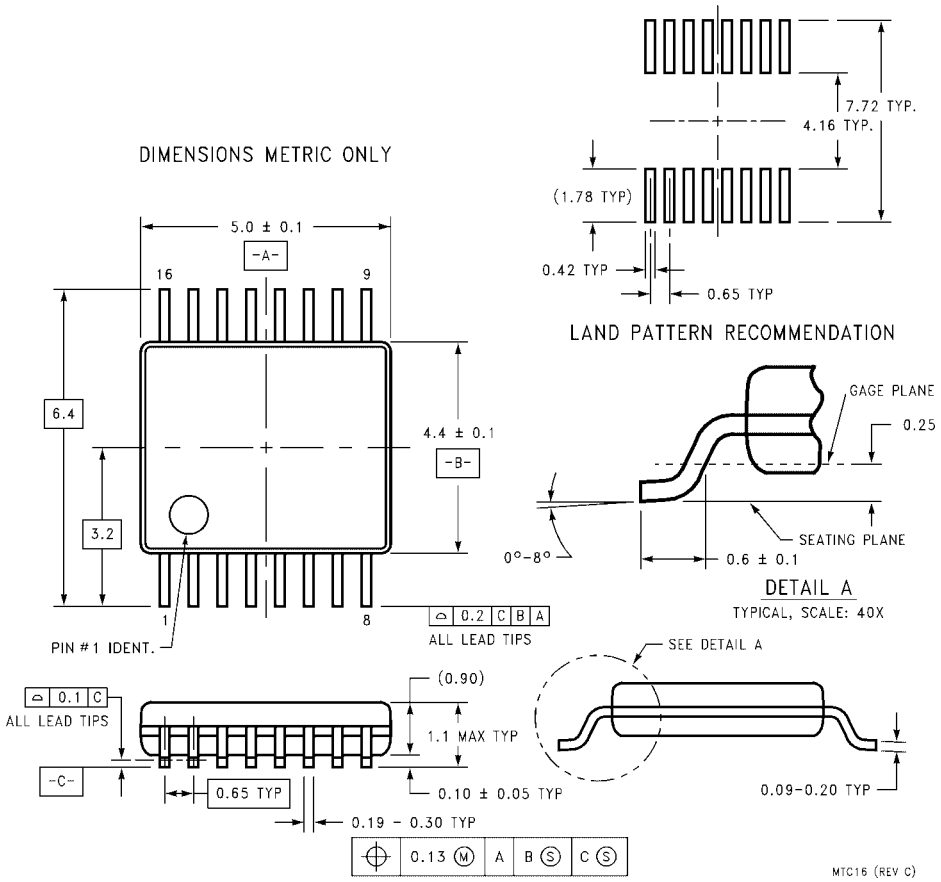
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

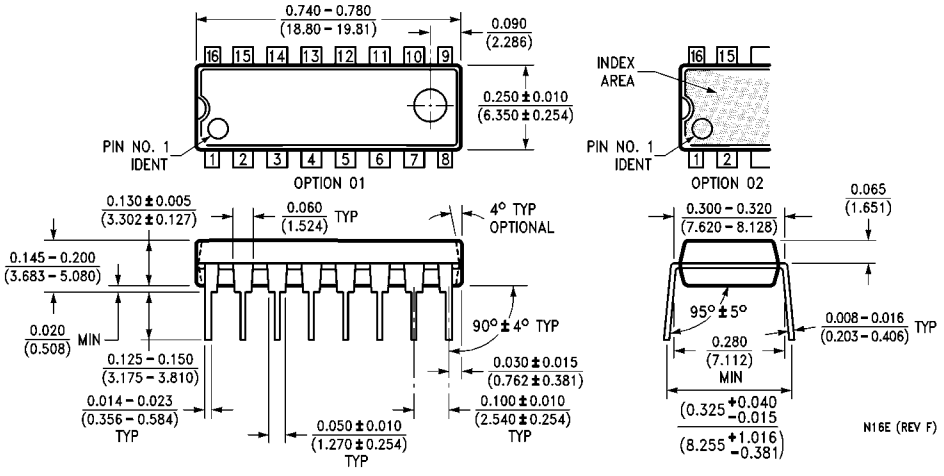
16-Lead Small Outline Package (SOIC), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC153 • 74ACT153
Dual 4-Input Multiplexer

General Description

The AC/ACT153 is a high-speed dual 4-input multiplexer with common select inputs and individual enable inputs for each section. It can select two lines of data from four sources. The two buffered outputs present data in the true (non-inverted) form. In addition to multiplexer operation, the AC/ACT153 can act as a function generator and generate any two functions of three variables.

Features

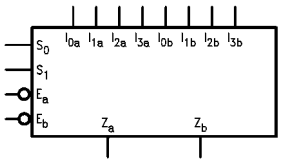
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- ACT153 has TTL-compatible inputs

Ordering Code:

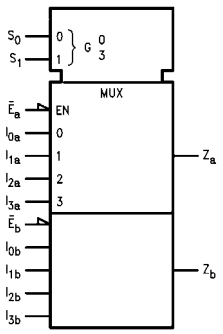
Order Number	Package Number	Package Description
74AC153SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC153SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC153MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC153PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT153SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT153MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

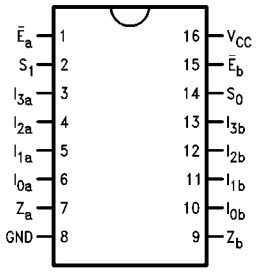
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{3a}	Side A Data Inputs
I_{0b}–I_{3b}	Side B Data Inputs
S_0, S_1	Common Select Inputs
$\overline{E}_a$	Side A Enable Input
$\overline{E}_b$	Side B Enable Input
Z_a	Side A Output
Z_b	Side B Output

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Functional Description

The AC/ACT153 is a dual 4-input multiplexer. It can select two bits of data from up to four sources under the control of the common Select inputs (S_0, S_1). The two 4-input multiplexer circuits have individual active-LOW Enables ($\overline{E}_a$, $\overline{E}_b$) which can be used to strobe the outputs independently. When the Enables ($\overline{E}_a$, $\overline{E}_b$) are HIGH, the corresponding outputs Z_a, Z_b) are forced LOW. The AC/ACT153 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the Select inputs. The logic equations for the outputs are shown below.

$$Z_a = \overline{E}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0)$$

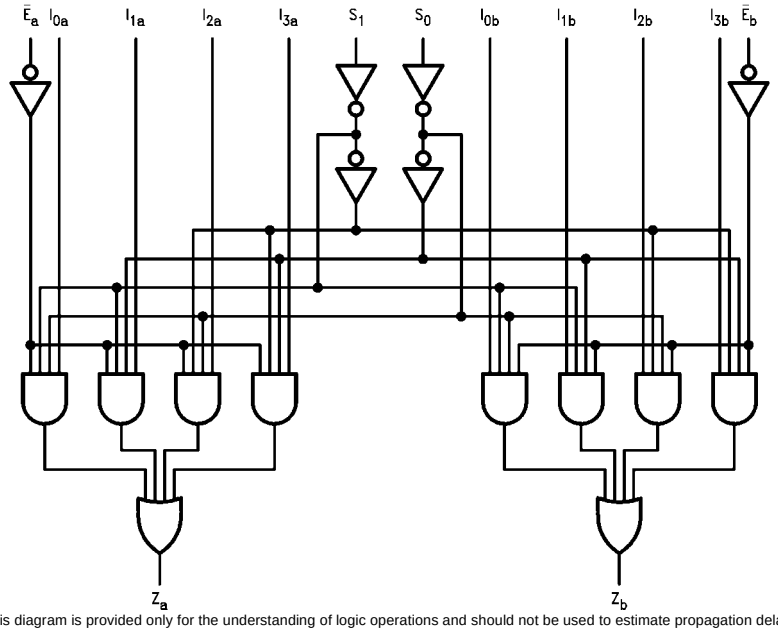
$$Z_b = \overline{E}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet \overline{S}_0 + I_{3b} \bullet S_1 \bullet S_0)$$

Truth Table

Select Inputs		Inputs (a or b)					Output
S_0	S_1	$\overline{E}$	I_0	I_1	I_2	I_3	Z
X	X	H	X	X	X	X	L
L	L	L	L	X	X	X	L
L	L	L	H	X	X	X	H
H	L	L	X	L	X	X	L
H	L	L	X	H	X	X	H
L	H	L	X	X	L	X	L
L	H	L	X	X	H	X	H
H	H	L	X	X	X	L	L
H	H	L	X	X	X	H	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
V_{IL}	Maximum LOW Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
V_{OH}	Minimum HIGH Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	$I_{OUT} = -50\ \mu A$
		4.5 5.5		3.86 4.86	3.76 4.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA $I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	$I_{OUT} = 50\ \mu A$
		4.5 5.5		0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA $I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay S_n to Z_n	3.3 5.0	2.5 2.0	9.5 6.5	15.0 11.0	2.5 2.0	17.5 12.5	ns
t_{PHL}	Propagation Delay S_n to Z_n	3.3 5.0	3.0 2.5	8.5 6.5	14.5 11.0	2.5 2.0	16.5 12.0	ns
t_{PLH}	Propagation Delay $\overline{E}$ to Z_n	3.3 5.0	2.5 1.5	8.0 5.5	13.5 9.5	2.0 1.5	16.0 11.0	ns
t_{PHL}	Propagation Delay $\overline{E}$ to Z_n	3.3 5.0	2.5 2.0	7.0 5.0	11.0 8.0	2.0 1.5	12.5 9.0	ns
t_{PLH}	Propagation Delay I_n to Z_n	3.3 5.0	2.5 1.5	7.5 5.5	12.5 9.0	2.0 1.5	14.5 10.5	ns
t_{PHL}	Propagation Delay I_n to Z_n	3.3 5.0	1.5 1.5	7.0 5.0	11.5 8.5	1.5 1.5	13.0 10.0	ns

Note 7: Voltage Range 3.3 is 3.3V ± 0 3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

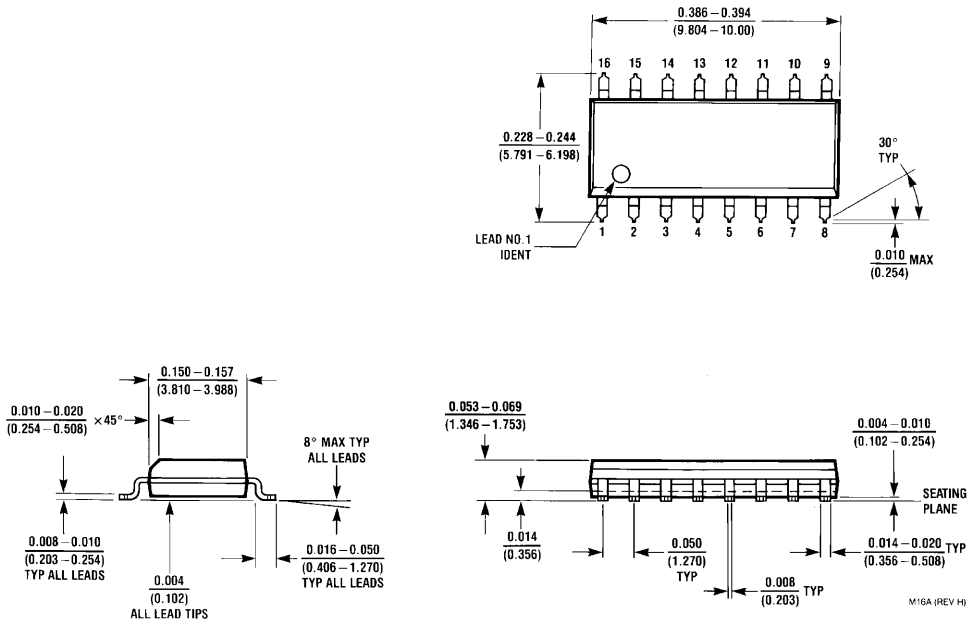
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z_n	5.0	3.0	7.0	11.5	2.0	13.5	ns
t_{PHL}	Propagation Delay S_n to Z_n	5.0	3.0	7.0	11.5	2.5	13.5	ns
t_{PLH}	Propagation Delay $\overline{E}_n$ to Z_n	5.0	2.0	6.5	10.5	2.0	12.5	ns
t_{PHL}	Propagation Delay $\overline{E}_n$ to Z_n	5.0	3.0	6.0	9.5	2.5	11.0	ns
t_{PLH}	Propagation Delay I_n to Z_n	5.0	2.5	5.5	9.5	2.0	11.0	ns
t_{PHL}	Propagation Delay I_n to Z_n	5.0	2.0	5.5	9.5	2.0	11.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

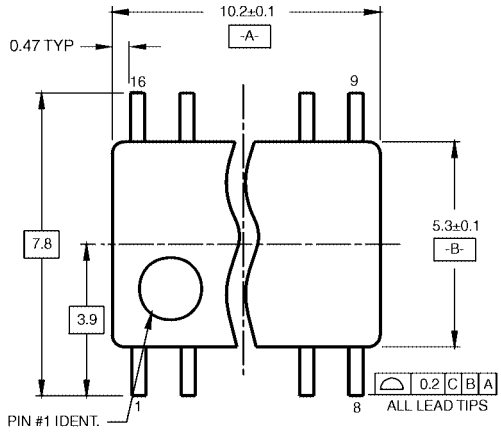
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	65.0	pF	V_{CC} = 5.0V

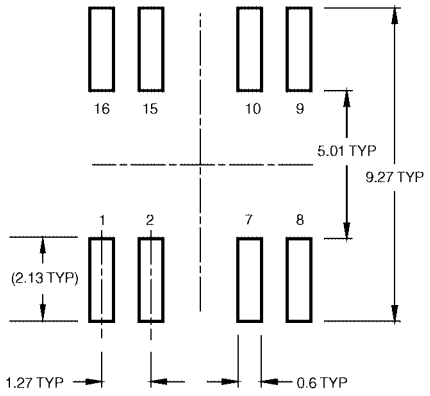
Physical Dimensions inches (millimeters) unless otherwise noted



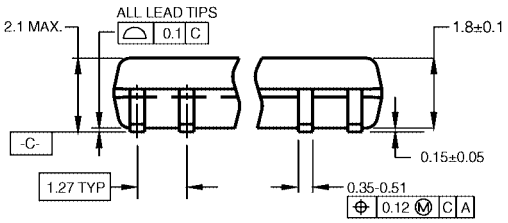
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

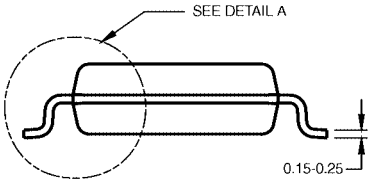
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



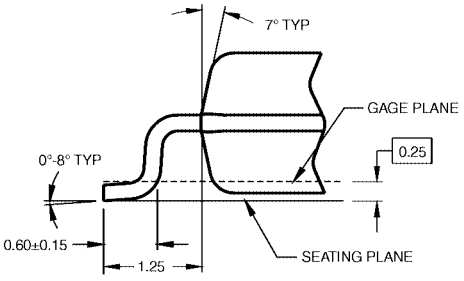


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

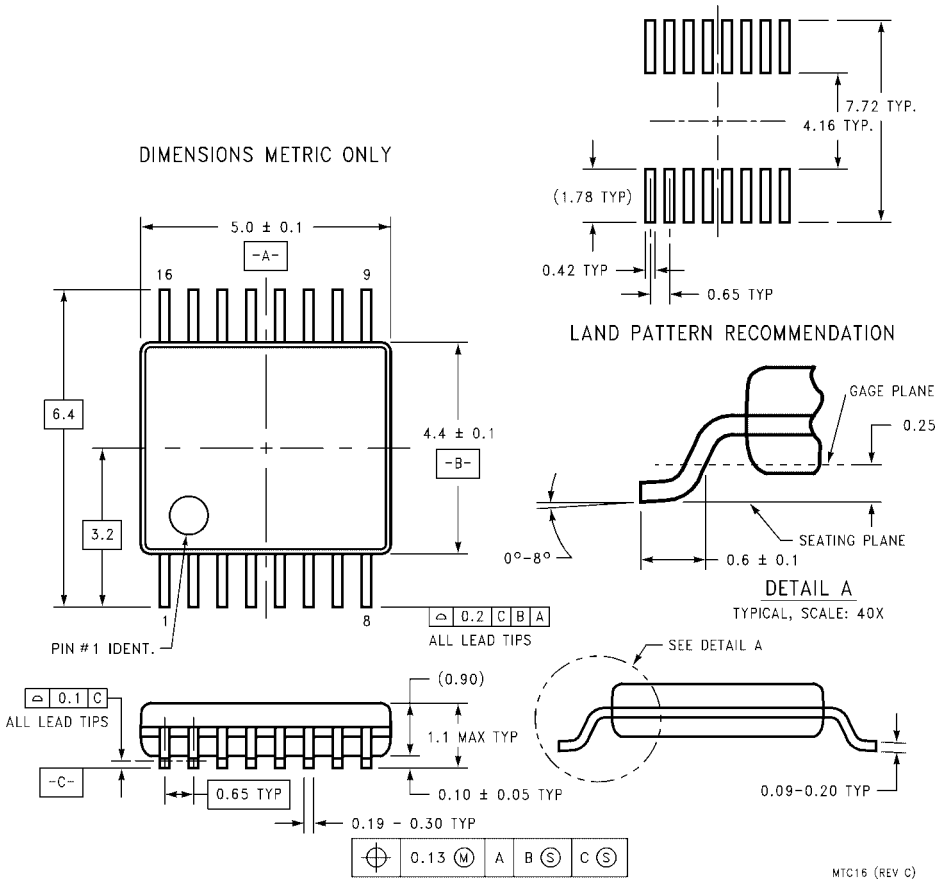
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

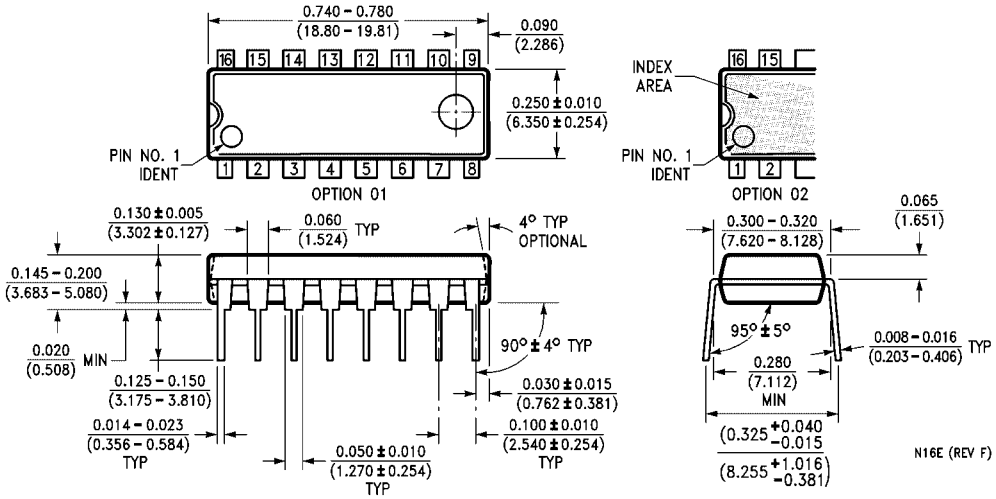
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC157 • 74ACT157
Quad 2-Input Multiplexer

General Description

The AC/ACT157 is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (noninverted) form. The AC/ACT157 can also be used as a function generator.

Features

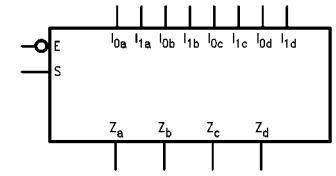
- I_{CC} and I_{OZ} reduced by 50%
- Outputs source/sink 24 mA
- ACT157 has TTL-compatible inputs

Ordering Code:

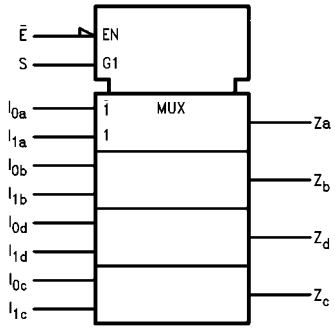
Order Number	Package Number	Package Description
74AC157SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74AC157SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC157MTC	MTC16	16 -Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC157PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT157SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74ACT157SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT157MTC	MTC16	16 -Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT157PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

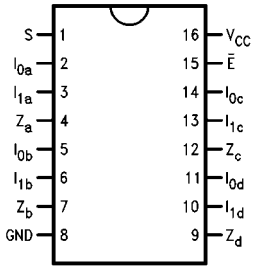
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{E}$	Enable Input
S	Select Input
Z_a–Z_d	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The AC/ACT157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\overline{E}$) is active-LOW. When $\overline{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The AC/ACT157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$$Z_a = \overline{E} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$$
$$Z_b = \overline{E} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$$
$$Z_c = \overline{E} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$$
$$Z_d = \overline{E} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$$

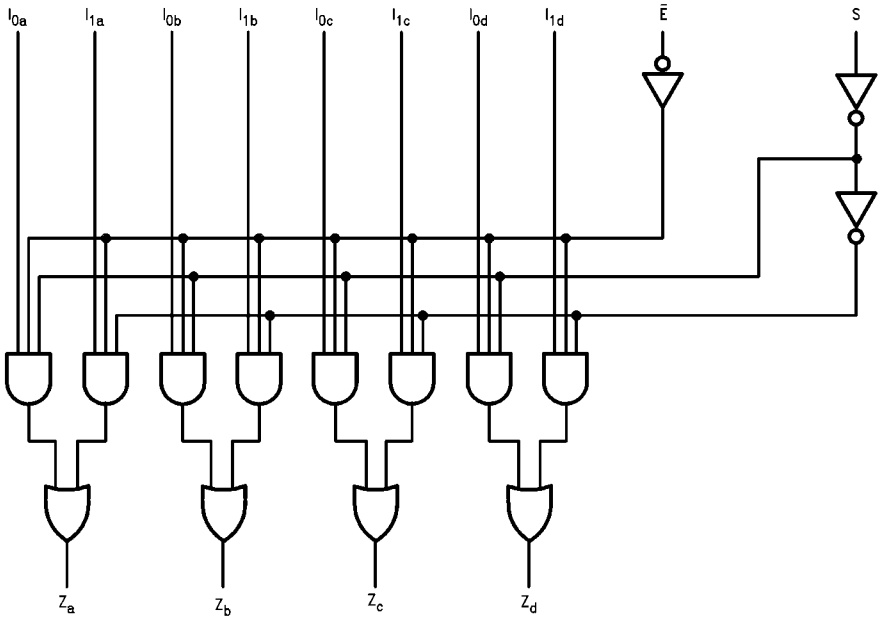
A common use of the AC/ACT157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The AC/ACT157 can generate any four of the sixteen different functions of two variables with one variable common. This is useful for implementing gating functions.

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay S to Z_n	3.3	1.5	7.0	11.5	1.5	13.0	ns
		5.0	1.5	5.5	9.0	1.5	10.0	
t_{PHL}	Propagation Delay S to Z_n	3.3	1.5	6.5	11.0	1.5	12.0	ns
		5.0	1.5	5.0	8.5	1.0	9.5	
t_{PLH}	Propagation Delay $\overline{E}$ to Z_n	3.3	1.5	7.0	11.5	1.5	13.0	ns
		5.0	1.5	5.5	9.0	1.5	10.0	
t_{PHL}	Propagation Delay $\overline{E}$ to Z_n	3.3	1.5	6.5	11.0	1.5	12.0	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t_{PLH}	Propagation Delay I_n to Z_n	3.3	1.5	5.0	8.5	1.0	9.0	ns
		5.0	1.5	4.0	6.5	1.0	7.0	
t_{PHL}	Propagation Delay I_n to Z_n	3.3	1.5	5.0	8.0	1.0	9.0	ns
		5.0	1.5	4.0	6.5	1.0	7.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

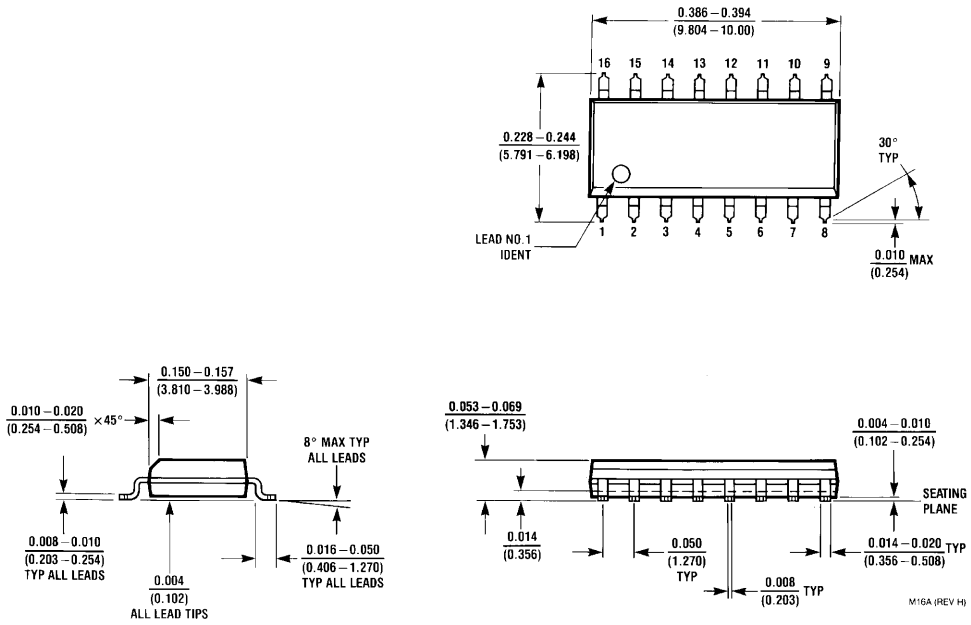
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S to Z_n	5.0	2.0	5.5	9.0	1.5	10.0	ns
t_{PHL}	Propagation Delay S to Z_n	5.0	2.0	5.5	9.5	2.0	10.5	ns
t_{PLH}	Propagation Delay $\overline{E}$ to Z_n	5.0	1.5	6.0	10.0	1.5	11.5	ns
t_{PHL}	Propagation Delay $\overline{E}$ to Z_n	5.0	1.5	5.0	8.5	1.0	9.0	ns
t_{PLH}	Propagation Delay I_n to Z_n	5.0	1.5	4.0	7.0	1.0	8.5	ns
t_{PHL}	Propagation Delay I_n to Z_n	5.0	1.5	4.5	7.5	1.0	8.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

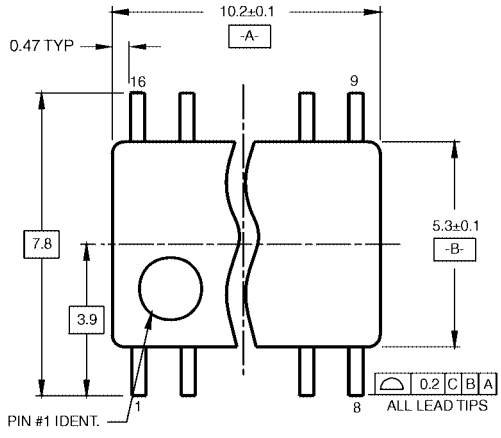
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	50.0	pF	V_{CC} = 5.0V

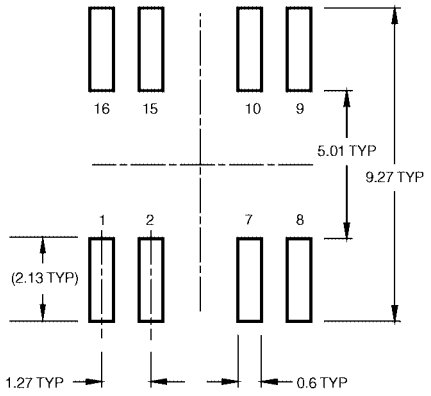
Physical Dimensions inches (millimeters) unless otherwise noted



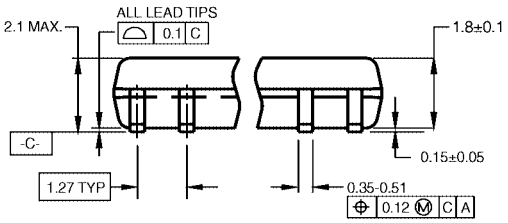
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

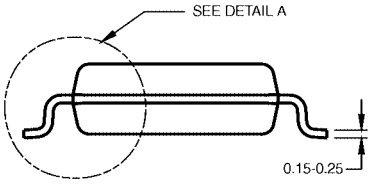
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



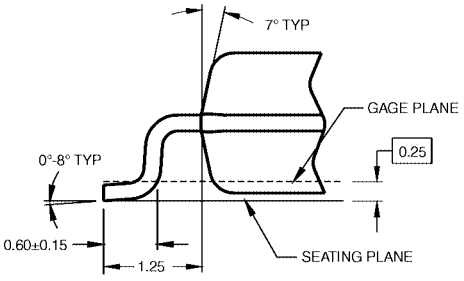


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

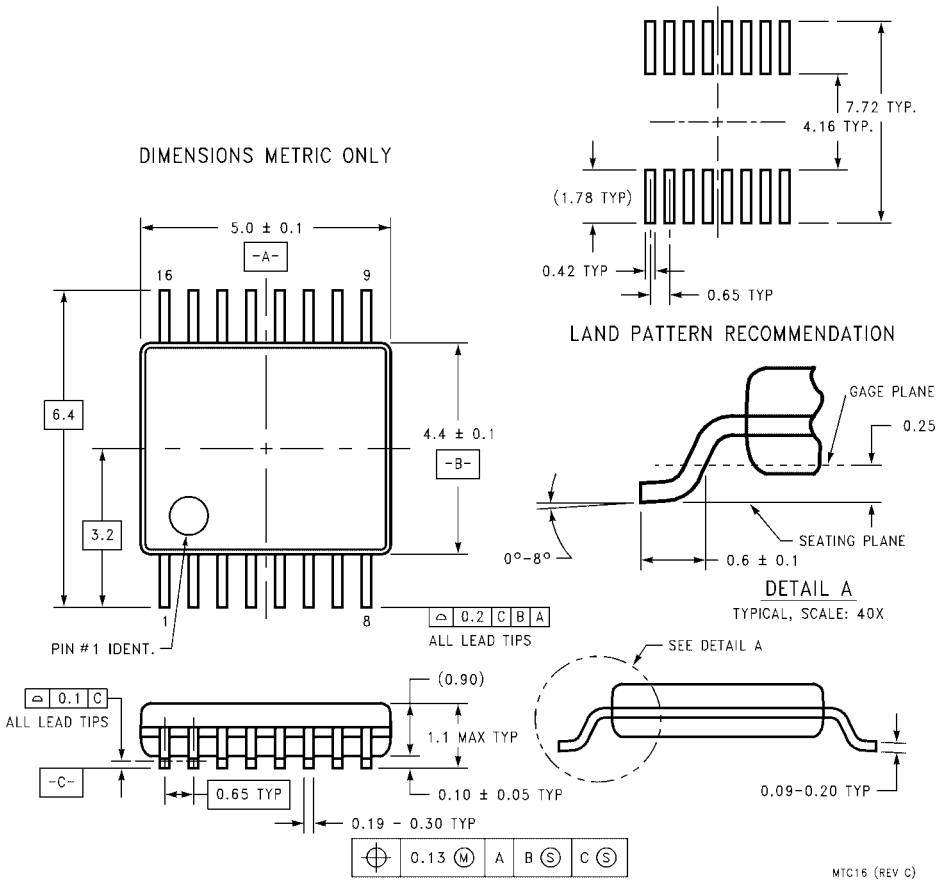
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

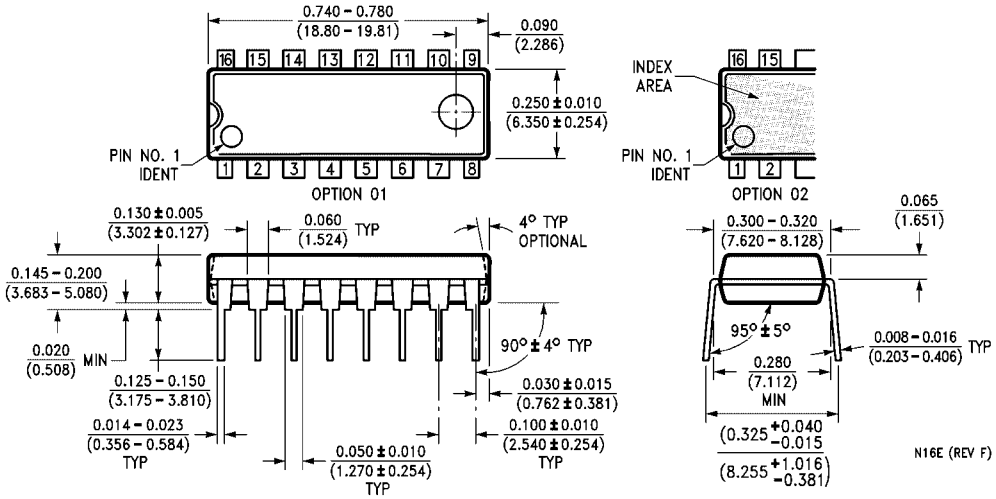
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16- Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC161 • 74ACT161
Synchronous Presettable Binary Counter

General Description

The AC/ACT161 are high-speed synchronous modulo-16 binary counters. They are synchronously presettable for application in programmable dividers and have two types of Count Enable inputs plus a Terminal Count output for versatility in forming synchronous multistage counters. The AC/ACT161 has an asynchronous Master Reset input that overrides all other inputs and forces the outputs LOW.

Features

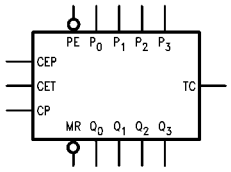
- I_{CC} reduced by 50%
- Synchronous counting and loading
- High-speed synchronous expansion
- Typical count rate of 125 MHz
- Outputs source/sink 24 mA
- ACT161 has TTL-compatible inputs

Ordering Code:

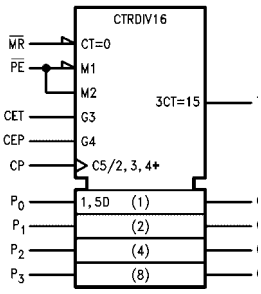
Order Number	Package Number	Package Description
74AC161SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC161SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC161MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC161PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT161SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT161SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT161MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT161PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

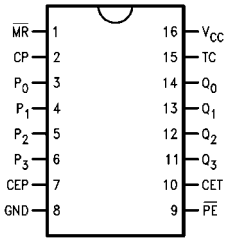
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
CEP	Count Enable Parallel Input
CET	Count Enable Trickle Input
CP	Clock Pulse Input
$\overline{MR}$	Asynchronous Master Reset Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Inputs
Q_0–Q_3	Flip-Flop Outputs
TC	Terminal Count Output

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The AC/ACT161 count in modulo-16 binary sequence. From state 15 (HHHH) they increment to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs (except due to Master Reset of the AC/ACT161) occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: asynchronous reset, parallel load, count-up and hold. Five control inputs—Master Reset, Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides all other inputs and asynchronously forces all outputs LOW. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{MR}$ HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The AC/ACT161 use D-type edge-triggered flip-flops and changing the $\overline{PE}$, CEP, and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 15. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to $\overline{TC}$ delay of the first stage, plus the cumulative $\overline{CET}$ to $\overline{TC}$ delays of the intermediate stages, plus the $\overline{CET}$ to CP setup time of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in Figure 2 are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle requires 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to $\overline{TC}$ delay of the first stage plus the $\overline{CEP}$ to CP setup time of the last stage. The $\overline{TC}$ output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters.

Logic Equations: Count Enable = CEP • CET • $\overline{PE}$

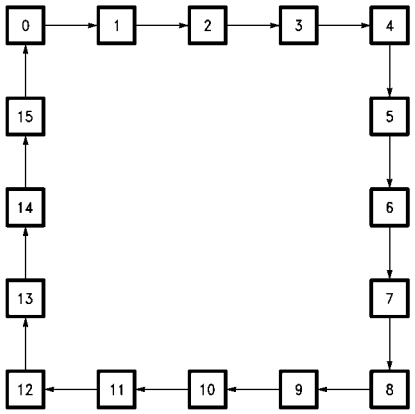
$TC = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet CET$

Mode Select Table

$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (↗)
X	X	X	Reset (Clear)
L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	Count (Increment)
H	L	X	No Change (Hold)
H	X	L	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagram



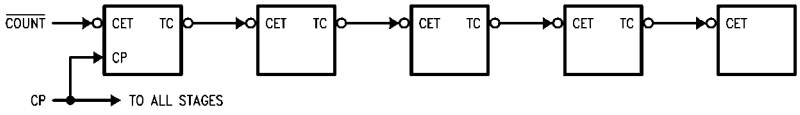


FIGURE 1. Multistage Counter with Ripple Carry

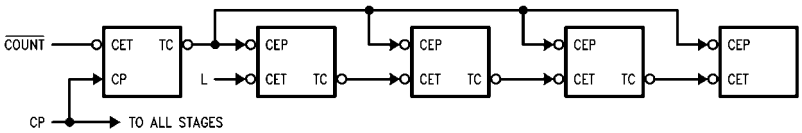
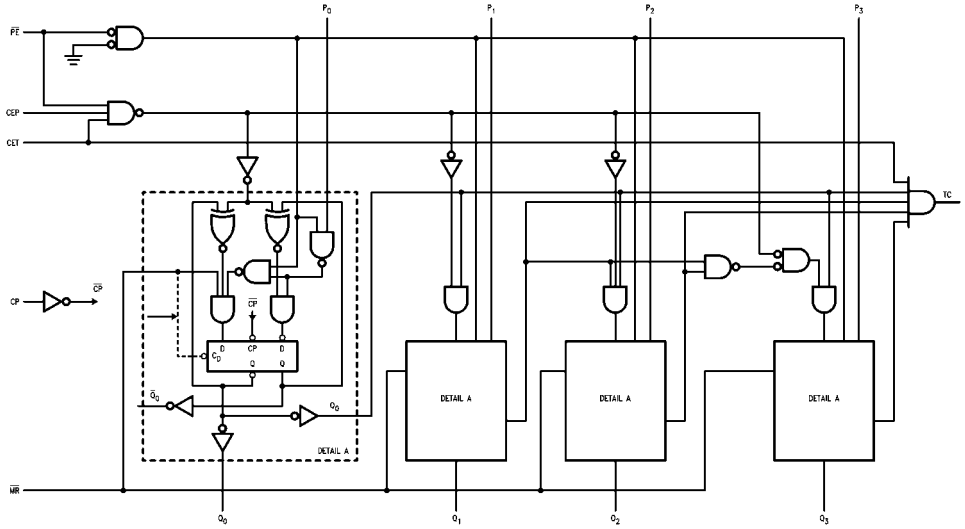


FIGURE 2. Multistage Counter with Lookahead Carry

Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT ™circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	3.3	70	111		60		MHz
		5.0	110	167		95		
t_{PLH}	Propagation Delay CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	3.3	2.0	7.0	12	1.5	13.5	ns
		5.0	1.5	5.0	9.0	1.0	9.5	
t_{PHL}	Propagation Delay CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	3.3	1.5	7.0	12	1.5	13	ns
		5.0	1.5	5.0	9.5	1.5	10	
t_{PLH}	Propagation Delay CP to TC	3.3	3.0	9	15	2.5	16.5	ns
		5.0	2.0	6	10.5	1.5	11.5	
t_{PHL}	Propagation Delay CP to TC	3.3	3.5	8.5	14	2.5	15.5	ns
		5.0	2.0	6.5	11	2.0	11.5	
t_{PLH}	Propagation Delay CET to TC	3.3	2.0	5.5	9.5	1.5	11	ns
		5.0	1.5	3.5	6.5	1.0	7.5	
t_{PHL}	Propagation Delay CET to TC	3.3	2.5	6.5	11	2.0	12.5	ns
		5.0	2.0	5	8.5	1.5	9.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	3.3	2.0	6.5	12	1.5	13.5	ns
		5.0	1.5	5.5	9.5	1.5	10	
t_{PHL}	Propagation Delay $\overline{MR}$ to TC	3.3	3.5	10	15	3.0	17.5	ns
		5.0	2.5	8.5	13	2.5	13.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	6.0	13.5	16	ns
	P_n to CP	5.0	3.5	8.5	10.5	
t_H	Hold Time, HIGH or LOW	3.3	−7.0	−1	−0.5	ns
	P_n to CP	5.0	−4.0	0	0	
t_S	Setup Time, HIGH or LOW	3.3	6.5	11.5	14	ns
	$\overline{PE}$ to CP	5.0	4.0	7.5	8.5	
t_H	Hold Time, HIGH or LOW	3.3	−6.0	0	0	ns
	$\overline{PE}$ to CP	5.0	−3.5	0.5	1	
t_S	Setup Time, HIGH or LOW	3.3	3.0	6.0	7	ns
	CEP or CET to CP	5.0	2.0	4.5	5	
t_H	Hold Time, HIGH or LOW	3.3	−3.5	0	0	ns
	CEP or CET to CP	5.0	−2	0	0.5	
t_W	Clock Pulse Width	3.3	2.0	3.5	4	ns
	(Load) HIGH or LOW	5.0	2.0	2.5	3	
t_W	Clock Pulse Width	3.3	2.0	4.0	4.5	ns
	(Count) HIGH or LOW	5.0	2.0	3.0	3.5	
t_W	$\overline{MR}$ Pulse Width,	3.3	3.0	5.5	7.5	ns
	LOW	5.0	2.5	4.5	6.0	
t_{REC}	Recovery Time		−2	−0.5	0	ns
	$\overline{MR}$ to CP		−1	0	0.5	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	5.0	115	125		100		MHz
t_{PLH}	Propagation Delay CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	5.0	1.5	5.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	5.0	1.5	6.0	10.5	1.5	11.5	ns
t_{PLH}	Propagation Delay CP to TC	5.0	2.0	7.0	11.0	1.5	12.5	ns
t_{PHL}	Propagation Delay CP to TC	5.0	1.5	8.0	12.5	1.5	13.5	ns
t_{PLH}	Propagation Delay CET to TC	5.0	1.5	5.5	8.5	1.5	10.0	ns
t_{PHL}	Propagation Delay CET to TC	5.0	1.5	6.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	1.5	6.0	10.0	1.5	11.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to TC	5.0	2.5	8.0	13.5	2.0	14.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

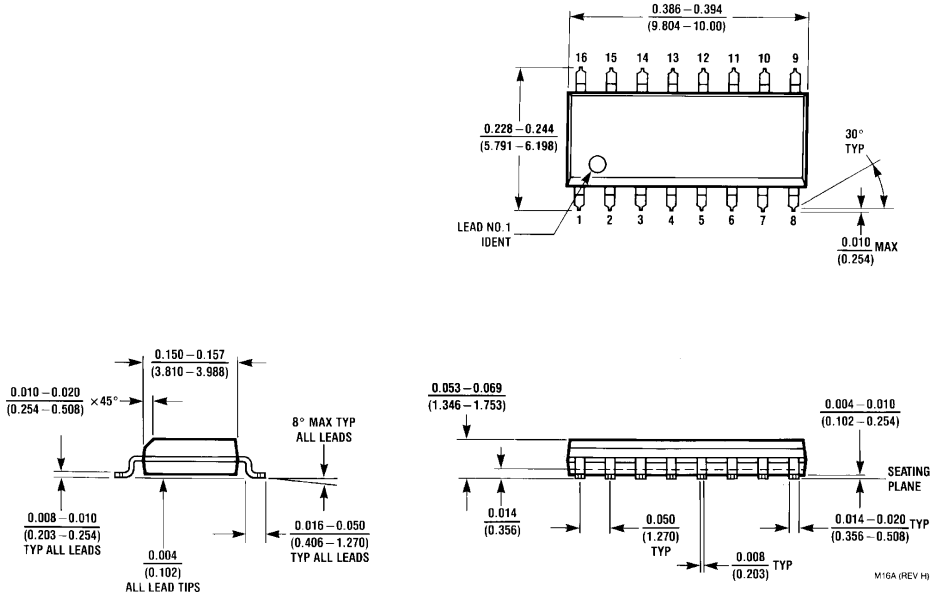
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW P_n to CP	5.0	4.0	9.5	11.5	ns
t_H	Hold Time, HIGH or LOW P_n to CP	5.0	−5.0	0	0	ns
t_S	Setup Time, HIGH or LOW $\overline{PE}$ to CP	5.0	4.0	8.5	9.5	ns
t_H	Hold Time, HIGH or LOW $\overline{PE}$ to CP	5.0	−5.5	−0.5	−0.5	ns
t_S	Setup Time, HIGH or LOW CEP or CET to CP	5.0	2.5	5.5	6.5	ns
t_H	Hold Time, HIGH or LOW CEP or CET to CP	5.0	−3.0	0	0	ns
t_W	Clock Pulse Width, (Load) HIGH or LOW	5.0	2.0	3.0	3.5	ns
t_W	Clock Pulse Width, (Count) HIGH or LOW	5.0	2.0	3.0	3.5	ns
t_W	$\overline{MR}$ Pulse Width, LOW	5.0	3.0	3.0	7.5	ns
t_{REC}	Recovery Time $\overline{MR}$ to CP	5.0	0	0	0.5	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

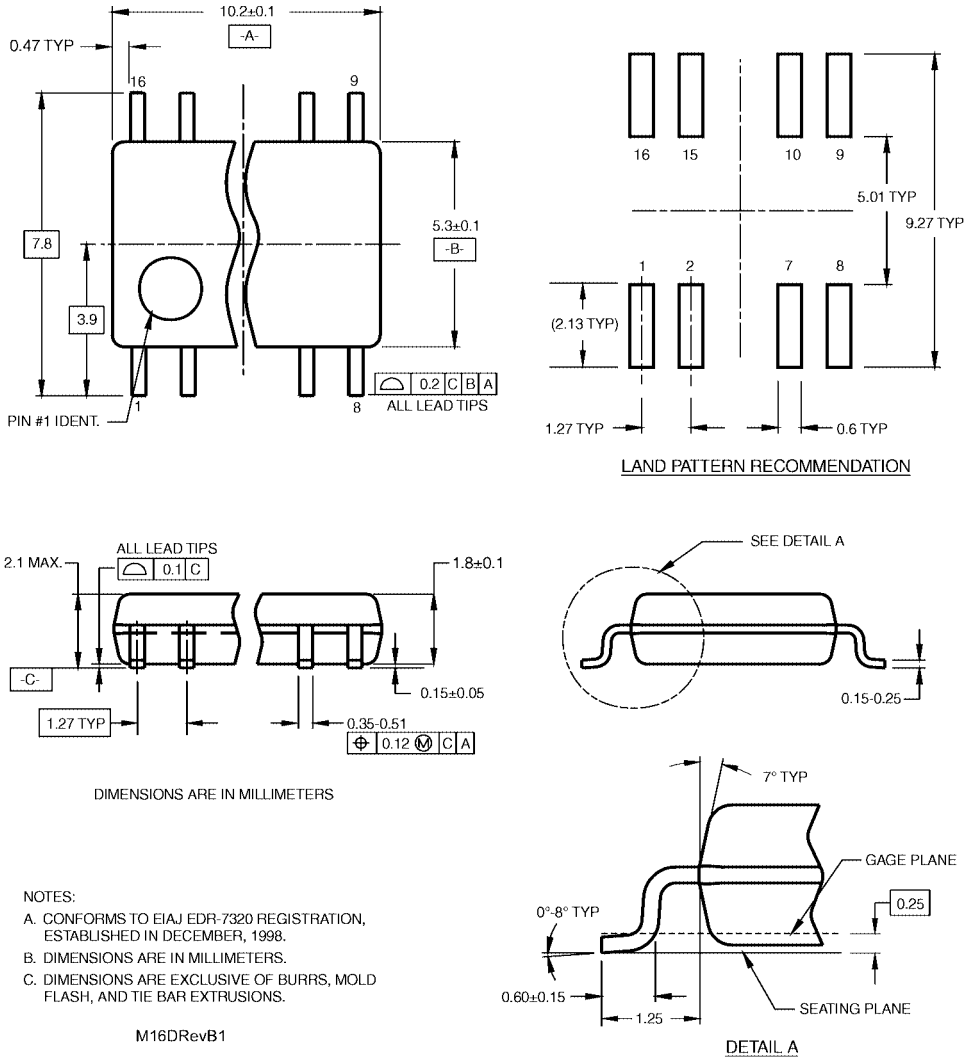
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

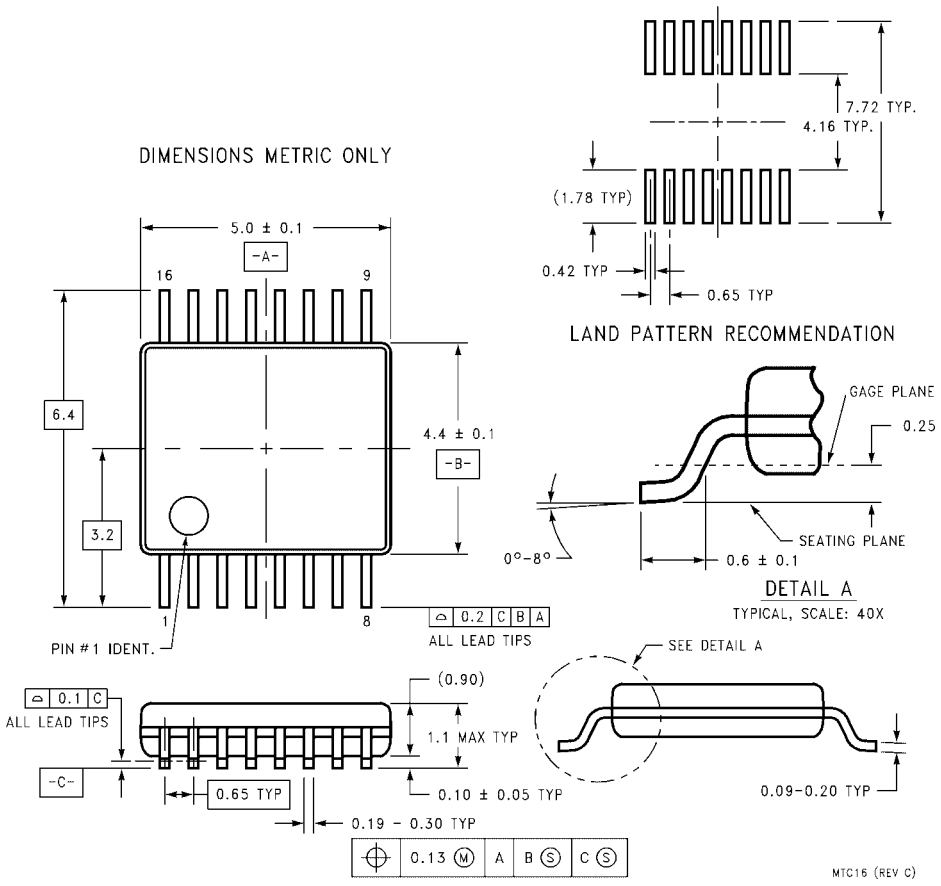
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

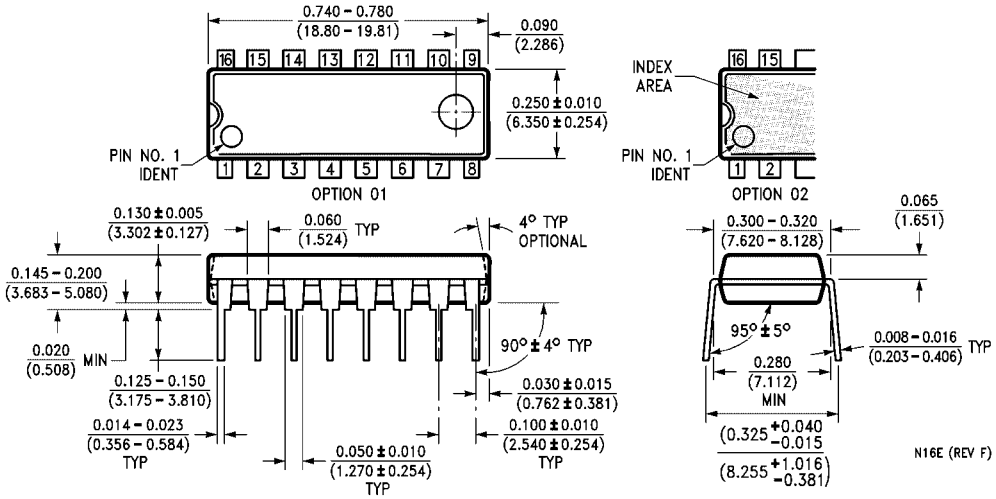
16- Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised February 2000

74AC163 • 74ACT163
Synchronous Presettable Binary Counter

General Description

The AC/ACT163 are high-speed synchronous modulo-16 binary counters. They are synchronously presettable for application in programmable dividers and have two types of Count Enable inputs plus a Terminal Count output for versatility in forming synchronous multistage counters. The AC/ACT163 has a Synchronous Reset input that overrides counting and parallel loading and allows the outputs to be simultaneously reset on the rising edge of the clock.

Features

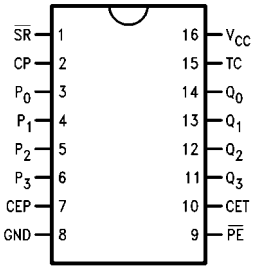
- I_{CC} reduced by 50%
- Synchronous counting and loading
- High-speed synchronous expansion
- Typical count rate of 125 MHz
- Outputs source/sink 24 mA
- ACT163 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC163SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC163SJ	M16D	16-Lead Small Outline Package, (SOP), EIAJ TYPE II, 5.3mm Wide
74AC163MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC163PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT163SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT163SJ	M16D	16-Lead Small Outline Package, (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT163MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT163PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

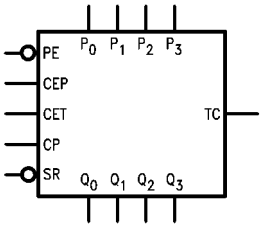
Connection Diagram



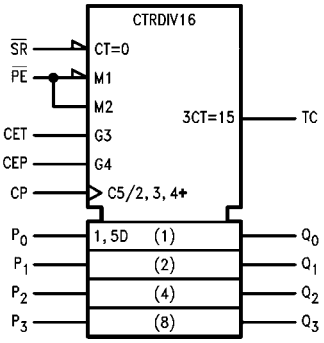
Pin Descriptions

Pin Names	Description
CEP	Count Enable Parallel Input
CET	Count Enable Trickle Input
CP	Clock Pulse Input
$\overline{SR}$	Synchronous Reset Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Input
Q_0–Q_3	Flip-Flop Outputs
TC	Terminal Count Output

Logic Symbols



IEEE/IEC



Mode Select Table

$\overline{SR}$	$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (⌐)
L	X	X	X	Reset (Clear)
H	L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	H	Count (Increment)
H	H	L	X	No Change (Hold)
H	H	X	L	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Description

The AC/ACT163 counts in modulo-16 binary sequence. From state 15 (HHHH) it increments to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: synchronous reset, parallel load, count-up and hold. Four control inputs—Synchronous Reset ($\overline{SR}$), Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{SR}$ overrides counting and parallel loading and allows all outputs to go LOW on the next rising edge of CP. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{SR}$ HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The AC/ACT163 uses D-type edge-triggered flip-flops and changing the $\overline{SR}$, $\overline{PE}$, CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 15. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to $\overline{TC}$ delay of the first stage, plus the cumulative $\overline{CET}$ to $\overline{TC}$ delays of the intermediate stages, plus the $\overline{CET}$ to CP setup time of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in Figure 2 are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle takes 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to $\overline{TC}$ delay of the first stage plus the $\overline{CEP}$ to CP setup time of the last stage. The $\overline{TC}$ output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters.

Logic Equations: Count Enable = CEP • CET • $\overline{PE}$

$TC = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet CET$

State Diagram

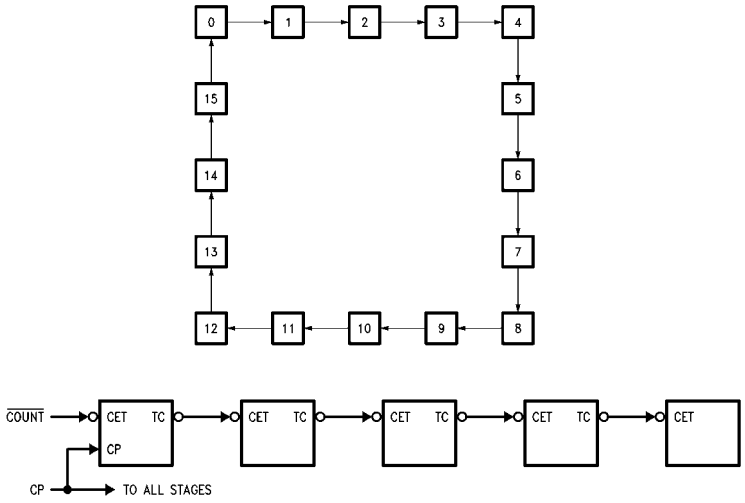


FIGURE 1.

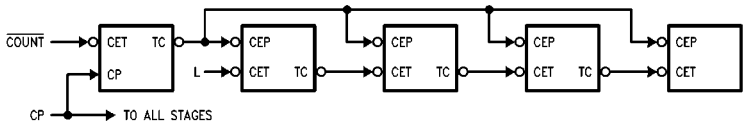
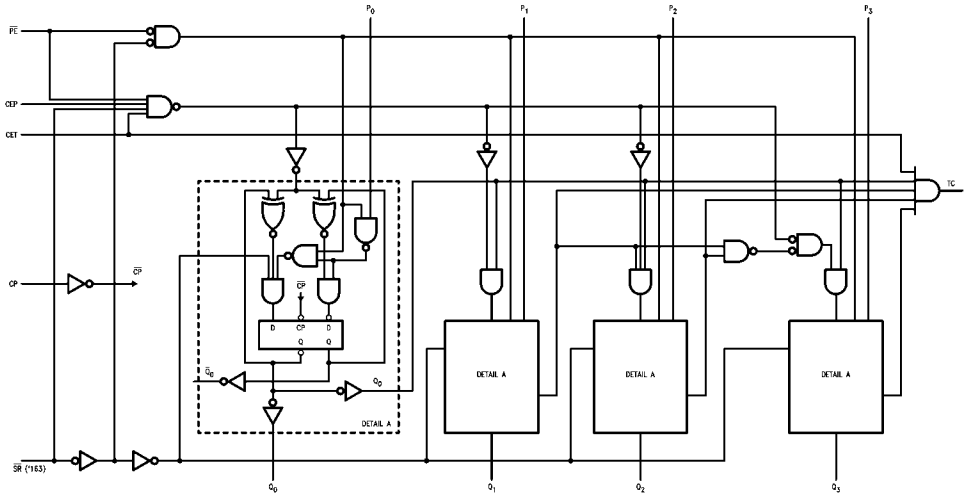


FIGURE 2.

Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL}or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent	5.5		4.0	40.0	μA	V_{IN} = V_{CC}
(Note 4)	Supply Current						or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	3.3	70	95		60		MHz
		5.0	110	140		95		
t_{PLH}	Propagation Delay, CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	3.3	2.0	7.5	12.5	1.5	13.5	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t_{PHL}	Propagation Delay, CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	3.3	1.5	8.5	12.0	1.5	13.0	ns
		5.0	1.5	6.0	9.5	1.5	10.0	
t_{PLH}	Propagation Delay CP to TC	3.3	3.0	9.5	15.0	2.5	16.5	ns
		5.0	2.0	7.0	10.5	1.5	11.5	
t_{PHL}	Propagation Delay CP to TC	3.3	3.5	11.0	14.0	2.5	15.5	ns
		5.0	2.0	8.0	11.0	2.0	11.5	
t_{PLH}	Propagation Delay CET to TC	3.3	2.0	7.5	9.5	1.5	11.0	ns
		5.0	1.5	5.5	6.5	1.0	7.5	
t_{PHL}	Propagation Delay CET to TC	3.3	2.5	8.5	11.0	2.0	12.5	ns
		5.0	2.0	6.0	8.5	1.5	9.5	

Note 7: Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF Typ	$T_A = +25°C$, $C_L = 50$ pF Guaranteed Minimum	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
t_S	Setup Time, HIGH or LOW	3.3	5.5	13.5	16.0	ns
	P_n to CP	5.0	4.0	8.5	10.5	
t_H	Hold Time, HIGH or LOW	3.3	−7.0	−1.0	−0.5	ns
	P_n to CP	5.0	−5.0	0	0	
t_S	Setup Time, HIGH or LOW	3.3	5.5	14.0	16.5	ns
	$\overline{SR}$ to CP	5.0	4.0	9.5	11.0	
t_H	Hold Time, HIGH or LOW	3.3	−7.5	−1.0	−0.5	ns
	$\overline{SR}$ to CP	5.0	−5.5	−0.5	0	
t_S	Setup Time, HIGH or LOW	3.3	5.5	11.5	14.0	ns
	$\overline{PE}$ to CP	5.0	4.0	7.5	8.5	
t_H	Hold Time, HIGH or LOW	3.3	−7.5	−1.0	−0.5	ns
	$\overline{PE}$ to CP	5.0	−5.0	−0.5	0	
t_S	Setup Time, HIGH or LOW	3.3	3.5	6.0	7.0	ns
	CEP or CET to CP	5.0	2.5	4.5	5.0	
t_H	Hold Time, HIGH or LOW	3.3	−4.5	0	0	ns
	CEP or CET to CP	5.0	−3.0	0	0.5	
t_W	Clock Pulse Width (Load)	3.3	3.0	3.5	4.0	ns
	HIGH or LOW	5.0	2.0	2.5	3.0	
t_W	Clock Pulse Width (Count)	3.3	3.0	4.0	4.5	ns
	HIGH or LOW	5.0	2.0	3.0	3.5	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	5.0	120	140		105		MHz
t_{PLH}	Propagation Delay, CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	5.0	1.5	5.5	10.0	1.5	11.0	ns
t_{PHL}	Propagation Delay, CP to Q_n ($\overline{PE}$ Input HIGH or LOW)	5.0	1.5	6.0	11.0	1.5	12.0	ns
t_{PLH}	Propagation Delay CP to TC	5.0	2.5	7.0	11.5	2.0	13.5	ns
t_{PHL}	Propagation Delay CP to TC	5.0	3.0	8.0	13.5	2.0	15.0	ns
t_{PLH}	Propagation Delay CET to TC	5.0	2.0	5.5	9.0	1.5	10.5	ns
t_{PHL}	Propagation Delay CET to TC	5.0	2.0	6.0	10.0	2.0	11.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

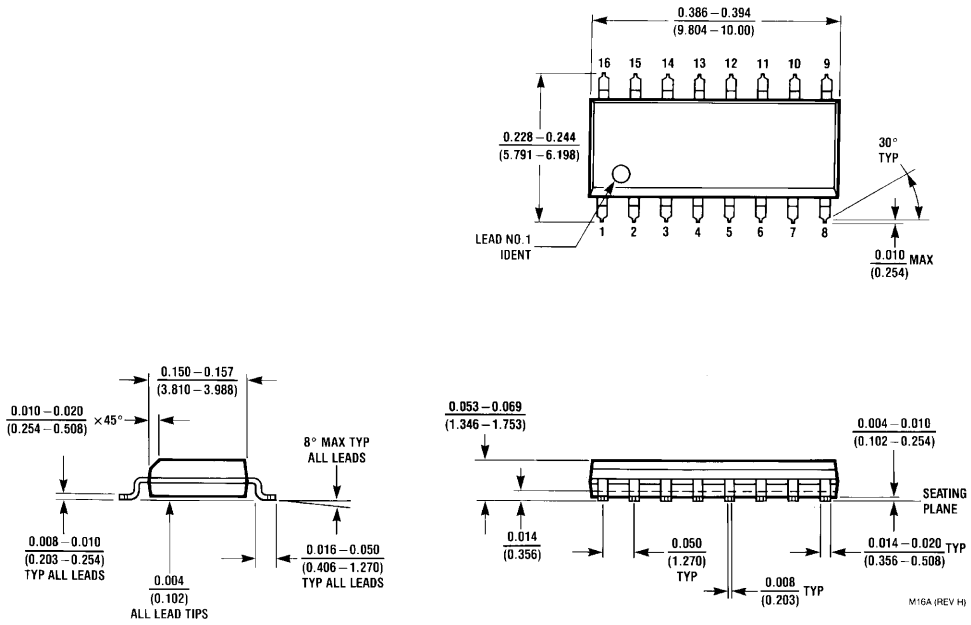
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW P_n to CP	5.0	4.0	10.0	12.0	ns
t_H	Hold Time, HIGH or LOW P_n to CP	5.0	–5.0	0.5	0.5	ns
t_S	Setup Time, HIGH or LOW $\overline{SR}$ to CP	5.0	4.0	10.0	11.5	ns
t_H	Hold Time, HIGH or LOW $\overline{SR}$ to CP	5.0	–5.5	–0.5	–0.5	ns
t_S	Setup Time, HIGH or LOW $\overline{PE}$ to CP	5.0	4.0	8.5	10.5	ns
t_H	Hold Time, HIGH or LOW $\overline{PE}$ to CP	5.0	–5.5	–0.5	0	ns
t_S	Setup Time, HIGH or LOW CEP or CET to CP	5.0	2.5	5.5	6.5	ns
t_H	Hold Time, HIGH or LOW CEP or CET to CP	5.0	–3.0	0	0.5	ns
t_W	Clock Pulse Width (Load) HIGH or LOW	5.0	2.0	3.5	3.5	ns
t_W	Clock Pulse Width (Count) HIGH or LOW	5.0	2.0	3.5	3.5	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

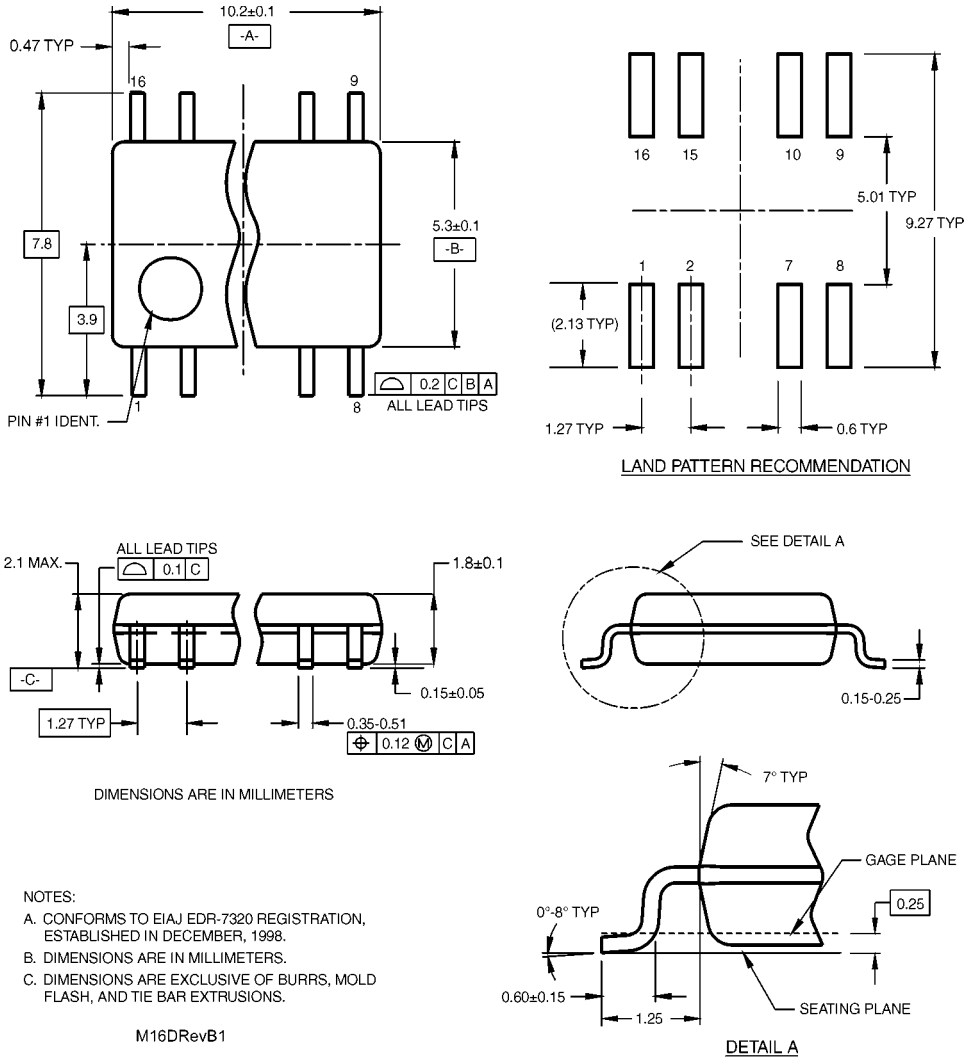
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

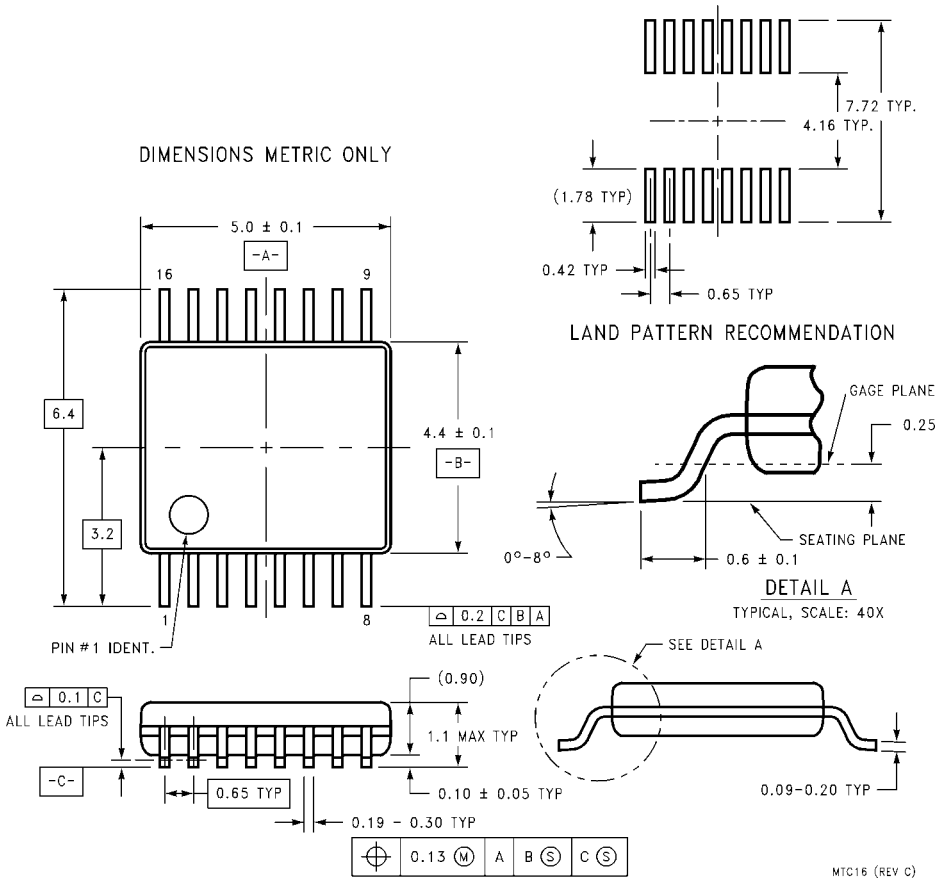
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

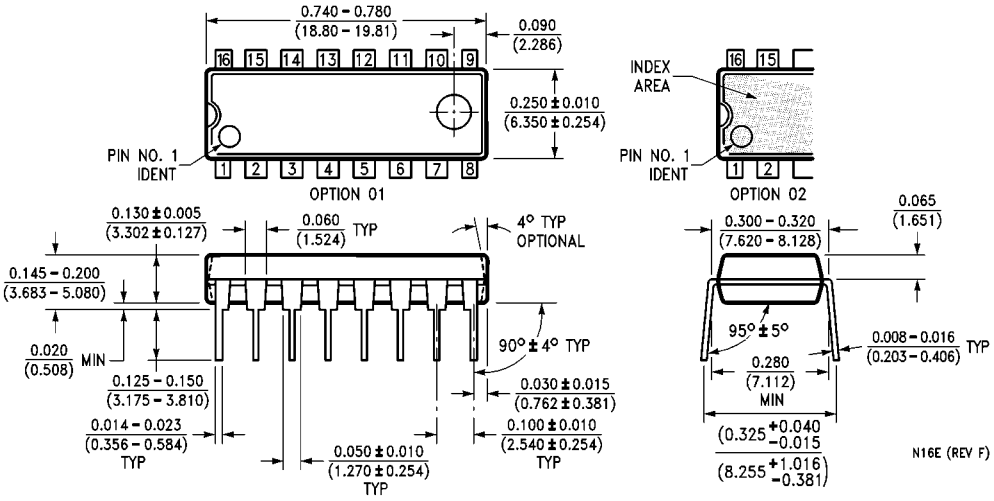
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC169
4-Stage Synchronous Bidirectional Counter

General Description

The AC169 is fully synchronous 4-stage up/down counter. The AC169 is a modulo-16 binary counter. It features a preset capability for programmable operation, carry lookahead for easy cascading and a U/$\overline{D}$ input to control the direction of counting. All state changes, whether in counting or parallel loading, are initiated by the LOW-to-HIGH transition of the Clock.

Features

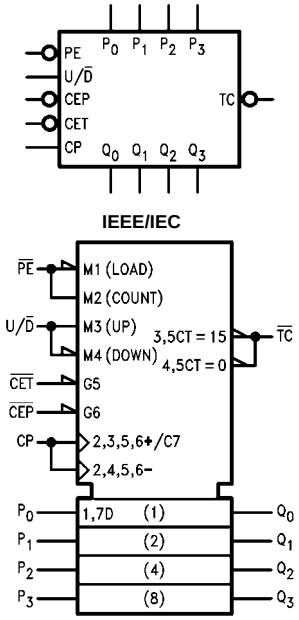
- I_{CC} reduced by 50%
- Synchronous counting and loading
- Built-In lookahead carry capability
- Presettable for programmable operation
- Outputs source/sink 24 mA

Ordering Code:

Order Number	Package Number	Package Description
74AC169SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC169SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC169MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC169PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

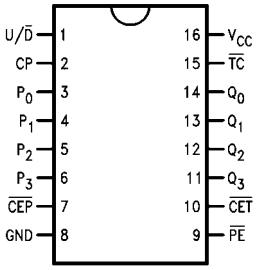
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{CEP}$	Count Enable Parallel Input
$\overline{CET}$	Count Enable Trickle Input
CP	Clock Pulse Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Input
U/$\overline{D}$	Up-Down Count Control Input
Q_0–Q_3	Flip-Flop Outputs
$\overline{TC}$	Terminal Count Output

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The AC169 uses edge-triggered J-K-type flip-flops and have no constraints on changing the control or data input signals in either state of the Clock. The only requirement is that the various inputs attain the desired state at least a setup time before the rising edge of the clock and remain valid for the recommended hold time thereafter. The parallel load operation takes precedence over the other operations, as indicated in the Mode Select Table. When $\overline{PE}$ is LOW, the data on the P_0–P_3 inputs enters the flip-flops on the next rising edge of the Clock. In order for counting to occur, both $\overline{CEP}$ and $\overline{CET}$ must be LOW and $\overline{PE}$ must be HIGH; the U/$\overline{D}$ input then determines the direction of counting. The Terminal Count ($\overline{TC}$) output is normally HIGH and goes LOW, provided that $\overline{CET}$ is LOW, when a counter reaches zero in the Count Down mode or reaches 15 in the Count Up mode. The $\overline{TC}$ output state is not a function of the Count Enable Parallel ($\overline{CEP}$) input level. If an illegal state occurs, the AC169 will return to the legitimate sequence within two counts. Since the $\overline{TC}$ signal is derived by decoding the flip-flop states, there exists the possibility of decoding spikes on $\overline{TC}$. For this reason the use of $\overline{TC}$ as a clock signal is not recommended (see logic equations below).

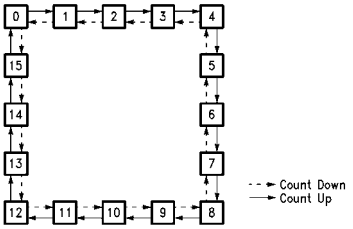
1. Count Enable = $\overline{CEP}$ •$\overline{CET}$ • $\overline{PE}$
2. Up: $\overline{TC}$ = Q_0•Q_1•$Q_2$$Q_3$•(Up)•$\overline{CET}$
3. Down: $\overline{TC}$ = $\overline{Q}_0$• $\overline{Q}_1$•$\overline{Q}_2$•$\overline{Q}_3$ •(Down)•$\overline{CET}$

Mode Select Table

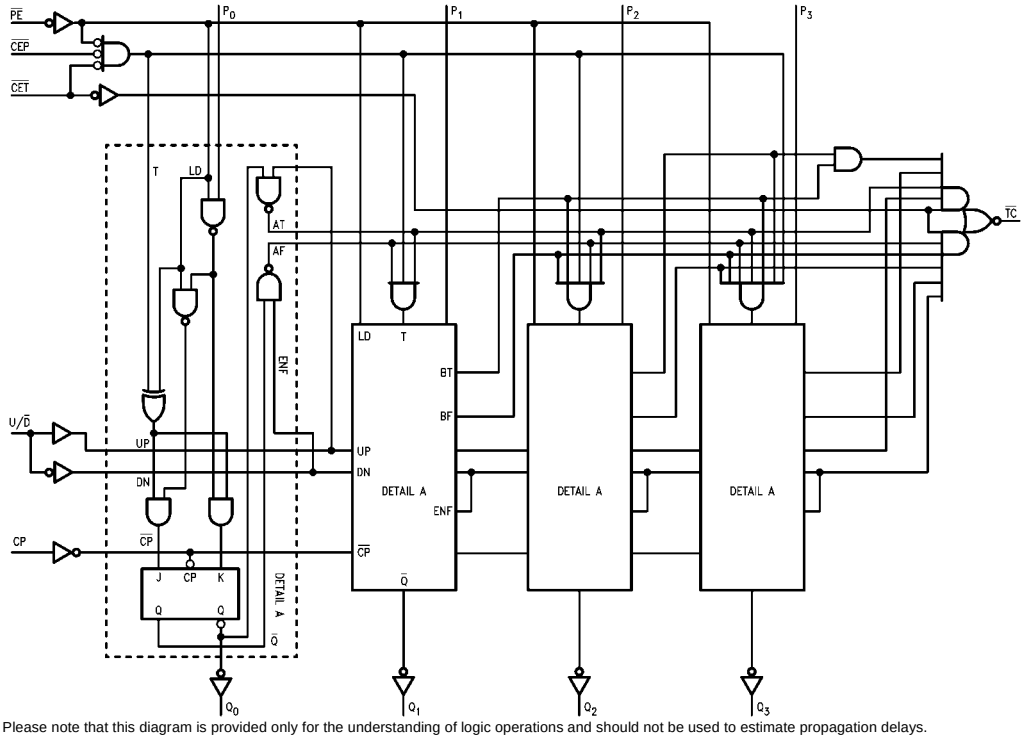
$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	U/$\overline{D}$	Action on Rising Clock Edge
L	X	X	X	Load (P_n to Q_n)
H	L	L	H	Count Up (Increment)
H	L	L	L	Count Down (Decrement)
H	H	X	X	No Change (Hold)
H	X	H	X	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagram



Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = –0.5V	–20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	–0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = –0.5V	–20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	–0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	–65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	–40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = –40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} – 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} – 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = –50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = –12 mA
		4.5		3.86	3.76	V	I_{OH} = –24 mA
		5.5		4.86	4.76		I_{OH} = –24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			–75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	3.3	75	118		65		MHz
		5.0	100	154		90		
t_{PLH}	Propagation Delay CP to Q_n ($\overline{PE}$ HIGH or LOW)	3.3	2.5	9.5	13.0	2.0	14.5	ns
		5.0	1.5	7.0	10.0	1.5	11.0	
t_{PHL}	Propagation Delay CP to Q_n ($\overline{PE}$ HIGH or LOW)	3.3	2.5	10.5	14.5	2.0	16.0	ns
		5.0	1.5	7.5	11.0	1.5	12.0	
t_{PLH}	Propagation Delay CP to $\overline{TC}$	3.3	4.5	13.5	18.0	3.5	22.0	ns
		5.0	3.0	9.5	13.0	2.0	14.0	
t_{PHL}	Propagation Delay CP to $\overline{TC}$	3.3	3.5	13.5	18.0	3.0	20.5	ns
		5.0	2.5	9.5	13.0	2.0	14.5	
t_{PLH}	Propagation Delay $\overline{CET}$ to $\overline{TC}$	3.3	3.5	11.0	15.0	3.0	16.5	ns
		5.0	3.0	8.0	10.5	2.5	12.0	
t_{PHL}	Propagation Delay $\overline{CET}$ to $\overline{TC}$	3.3	3.0	9.5	12.5	2.5	14.5	ns
		5.0	2.0	7.0	9.0	1.5	10.0	
t_{PLH}	Propagation Delay U/$\overline{D}$ to $\overline{TC}$	3.3	3.5	11.0	15.0	3.0	17.0	ns
		5.0	2.5	8.0	10.5	2.0	12.0	
t_{PHL}	Propagation Delay U/$\overline{D}$ to $\overline{TC}$	3.3	2.5	10.0	13.5	2.0	15.5	ns
		5.0	1.5	7.0	9.5	1.5	10.5	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements

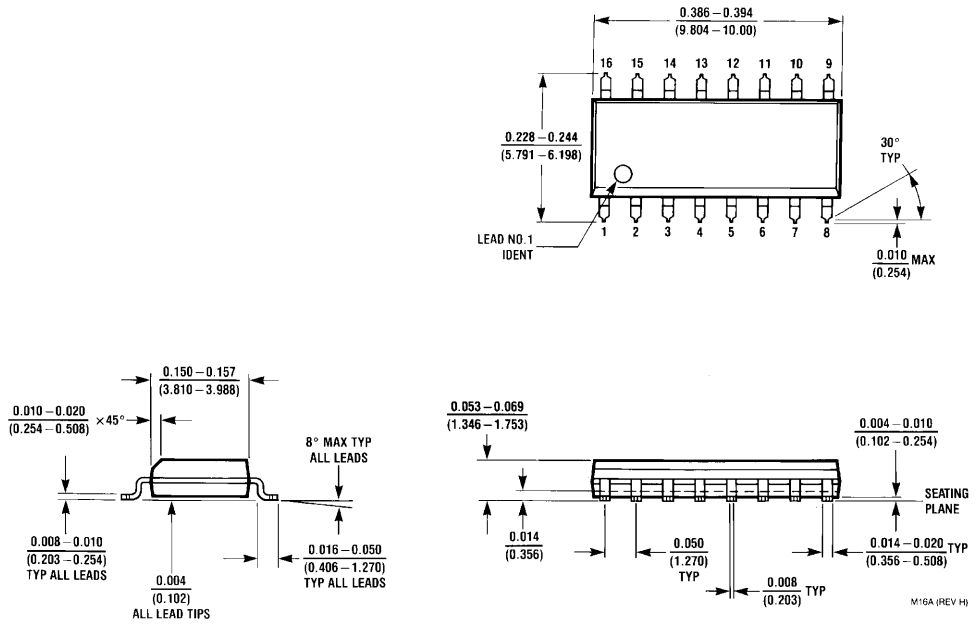
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW P_n to CP	3.3	3.0	4.5	5.0	ns
		5.0	1.5	2.5	2.5	
t_H	Hold Time, HIGH or LOW P_n to CP	3.3	–1.5	0.5	0.5	ns
		5.0	–0.5	1.5	1.5	
t_S	Setup Time, HIGH or LOW $\overline{CEP}$ to CP	3.3	7.5	10.5	12.5	ns
		5.0	4.5	7.0	8.0	
t_H	Hold Time, HIGH or LOW $\overline{CEP}$ to CP	3.3	–4.5	0	0	ns
		5.0	–2.0	0.5	1.0	
t_S	Setup Time, HIGH or LOW $\overline{CET}$ to CP	3.3	7.0	10.0	12.0	ns
		5.0	4.0	6.5	8.0	
t_H	Hold Time, HIGH or LOW $\overline{CET}$ to CP	3.3	–6.0	0	0	ns
		5.0	–4.0	0.5	1.0	
t_S	Setup Time, HIGH or LOW $\overline{PE}$ to CP	3.3	3.5	5.5	6.5	ns
		5.0	2.0	3.5	4.0	
t_H	Hold Time, HIGH or LOW $\overline{PE}$ to CP	3.3	–3.5	0	0	ns
		5.0	–1.5	0.5	0.5	
t_S	Setup Time, HIGH or LOW U/$\overline{D}$ to CP	3.3	7.0	10.0	11.5	ns
		5.0	4.5	6.5	7.5	
t_H	Hold Time, HIGH or LOW U/$\overline{D}$ to $\overline{CP}$	3.3	–7.0	0	0	ns
		5.0	–4.0	0.5	0.5	
t_W	CP Pulse Width, HIGH or LOW	3.3	2.0	3.0	4.0	ns
		5.0	2.0	3.0	3.0	

Note 6: Voltage Range 3.3 is 3.3V ± 0.3V Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

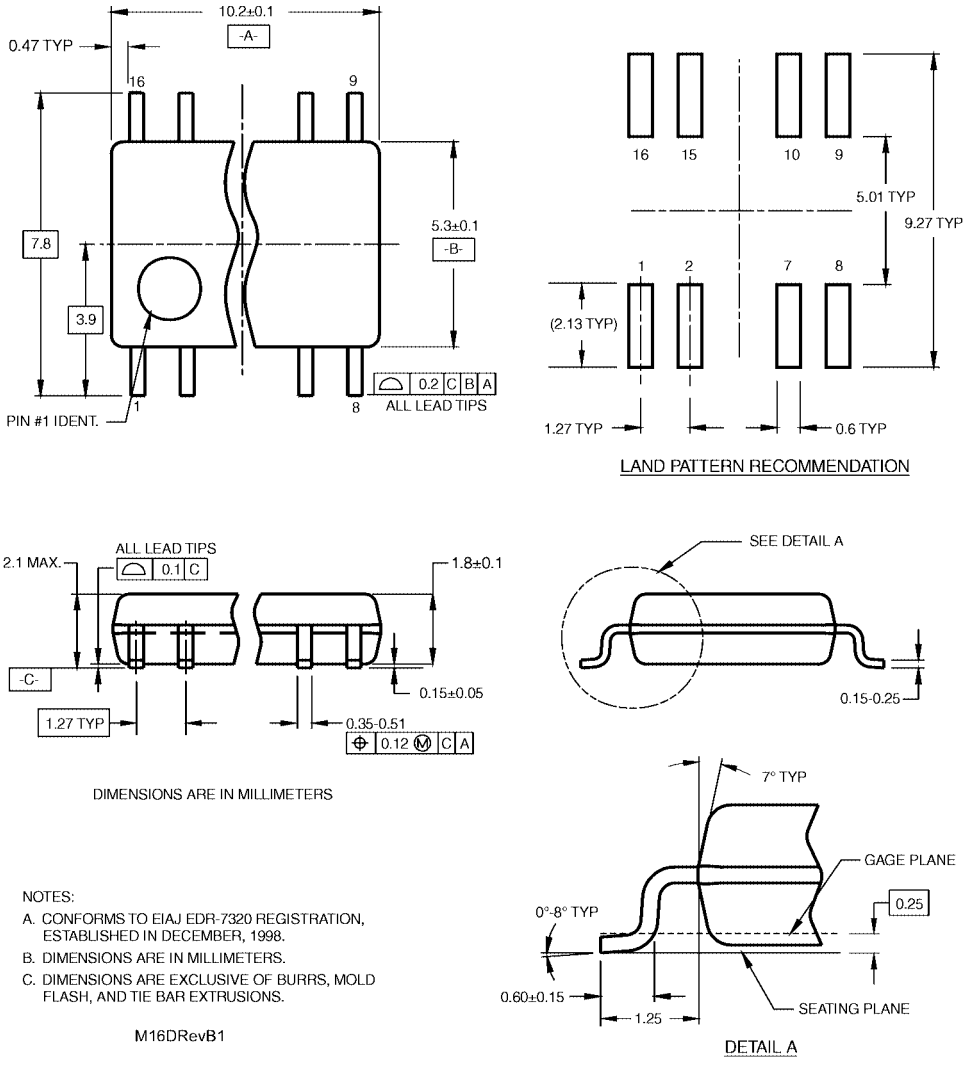
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	60.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 1.150" Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

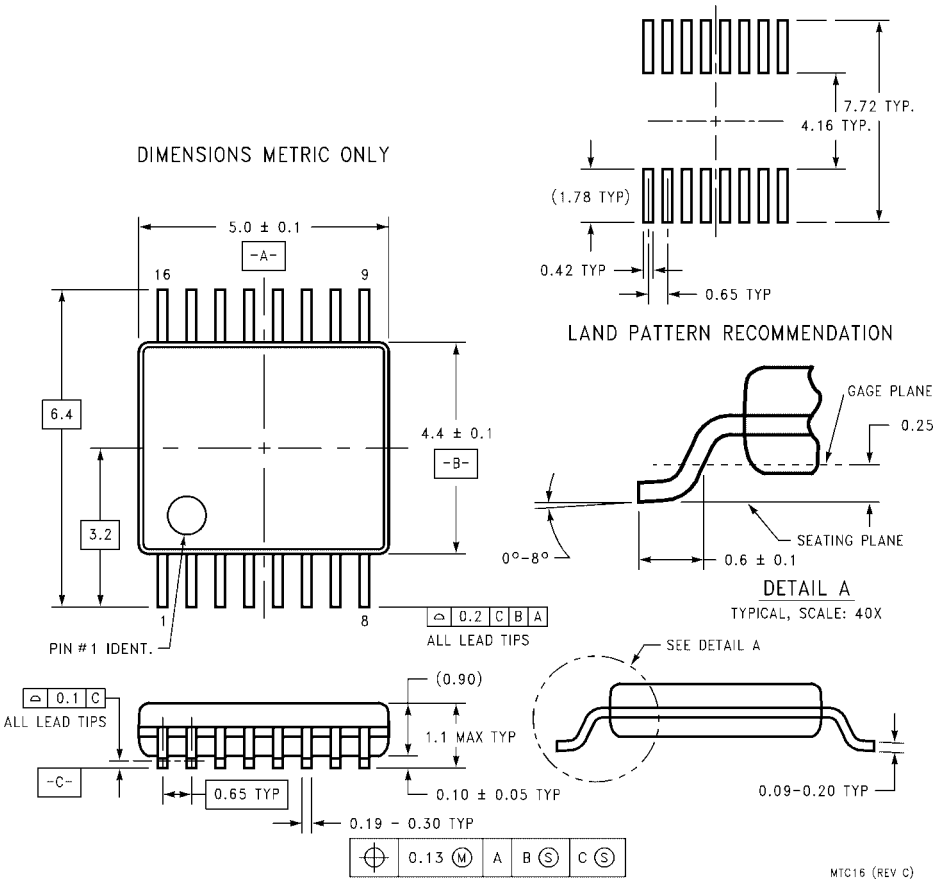
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

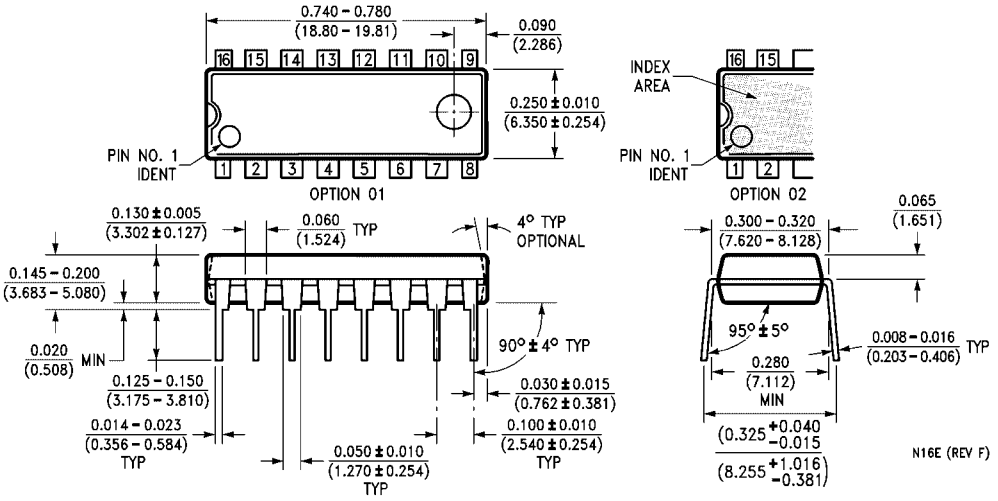
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC174 • 74ACT174
Hex D-Type Flip-Flop with Master Reset

General Description

The AC/ACT174 is a high-speed hex D-type flip-flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the LOW-to-HIGH clock transition. The device has a Master Reset to simultaneously clear all flip-flops.

Features

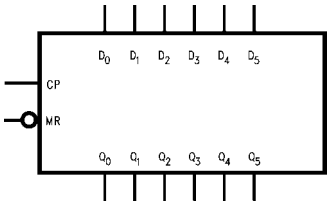
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- ACT174 has TTL-compatible inputs

Ordering Code:

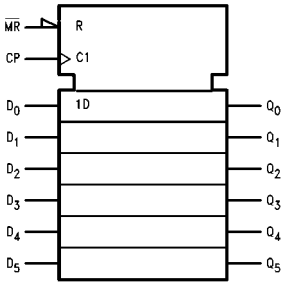
Order Number	Package Number	Package Description
74AC174SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74AC174SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC174PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT174SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow
74ACT174SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT174MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT174PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

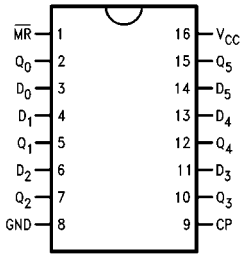
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_5	Data Inputs
CP	Clock Pulse Input
$\overline{MR}$	Master Reset Input
Q_0–Q_5	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

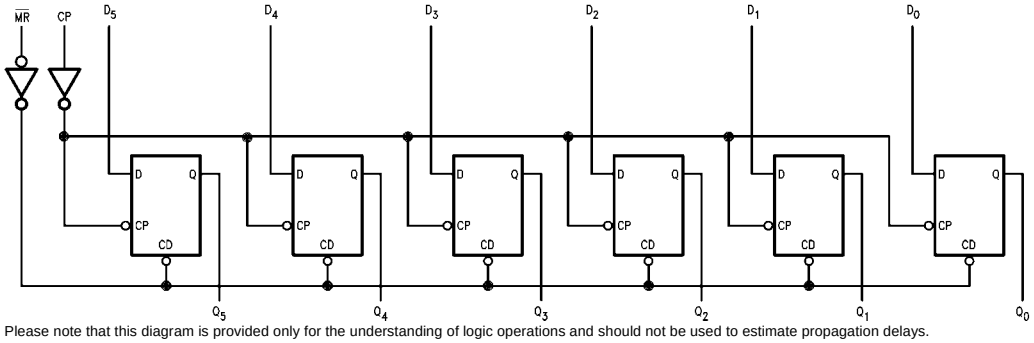
The AC/ACT174 consists of six edge-triggered D-type flip-flops with individual D inputs and Q outputs. The Clock (CP) and Master Reset ($\overline{MR}$) are common to all flip-flops. Each D input's state is transferred to the corresponding flip-flop's output following the LOW-to-HIGH Clock (CP) transition. A LOW input to the Master Reset ($\overline{MR}$) will force all outputs LOW independent of Clock or Data inputs. The AC/ACT174 is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Truth Table

Inputs			Output
$\overline{MR}$	CP	D	Q
L	X	X	L
H	⌐	H	H
H	⌐	L	L
H	L	X	Q

H = HIGH Voltage Level
L = LOW Voltage Level
⌐ = LOW-to-HIGH Transition
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC}	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	2.0	2.0		or $V_{CC} - 0.1V$
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	0.8	0.8		or $V_{CC} - 0.1V$
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
	Output Voltage	5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
	Output Voltage	5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock	3.3	90	100		70		MHz
	Frequency	5.0	100	125		100		
t_{PLH}	Propagation Delay	3.3	2.0	9.0	11.5	1.5	12.5	ns
	CP to Q_n	5.0	1.5	6.0	8.5	1.0	9.5	
t_{PHL}	Propagation Delay	3.3	2.0	8.5	11.0	1.5	12.0	ns
	CP to Q_n	5.0	1.5	6.0	8.0	1.0	9.0	
t_{PHL}	Propagation Delay	3.3	2.5	9.0	11.5	2.0	12.5	ns
	$\overline{MR}$ to Q_n	5.0	1.5	7.0	9.0	1.5	10.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	2.5	6.5	7.0	ns
	D_n to CP	5.0	2.0	5.0	5.5	
t_H	Hold Time, HIGH or LOW	3.3	1.0	3.0	3.0	ns
	D_n to CP	5.0	0.5	3.0	3.0	
t_W	$\overline{MR}$ Pulse Width, LOW	3.3	1.0	5.5	7.0	ns
		5.0	1.0	5.0	5.0	
t_W	CP Pulse Width	3.3	1.0	5.5	7.0	ns
		5.0	1.0	5.0	5.0	
t_{REC}	Recovery Time	3.3	0	2.5	2.5	ns
	$\overline{MR}$ to CP	5.0	0	2.0	2.0	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	165	200		140		MHz
t_{PLH}	Propagation Delay CP to Q_n	5.0	1.5	7.0	10.5	1.5	11.5	ns
t_{PHL}	Propagation Delay CP to Q_n	5.0	1.5	7.0	10.5	1.5	11.5	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	1.5	6.5	9.5	1.5	11.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

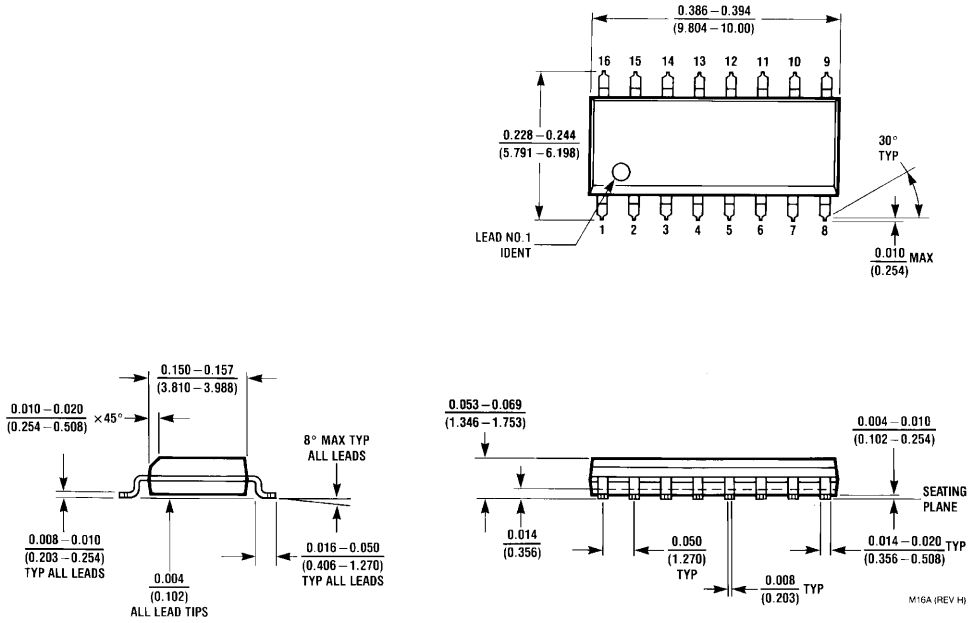
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	0.5	1.5	1.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	1.0	2.0	2.0	ns
t_W	$\overline{MR}$ Pulse Width, LOW	5.0	1.5	3.0	3.5	ns
t_W	CP Pulse Width, HIGH or LOW	5.0	1.5	3.0	3.5	ns
t_{rec}	Recovery Time $\overline{MR}$ to CP	5.0	–1.0	0.5	0.5	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

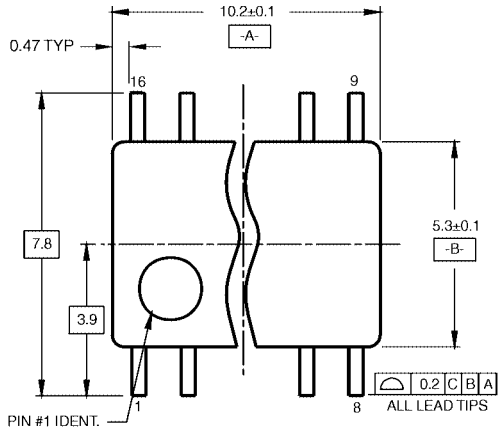
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	85.0	pF	V_{CC} = 5.0V

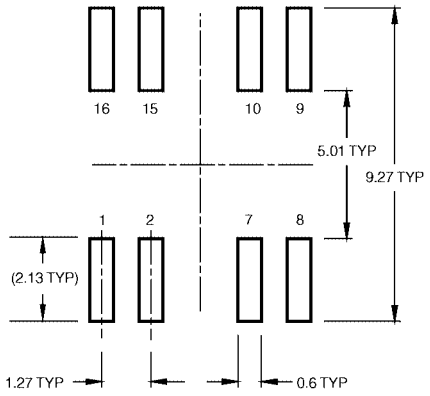
Physical Dimensions inches (millimeters) unless otherwise noted



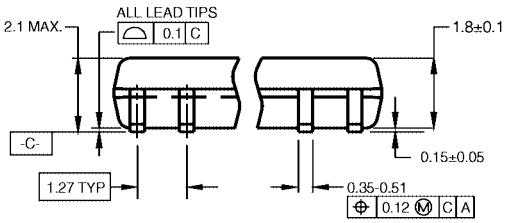
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

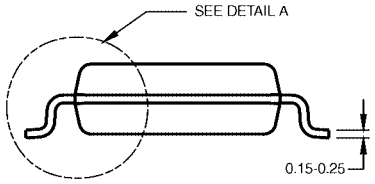
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

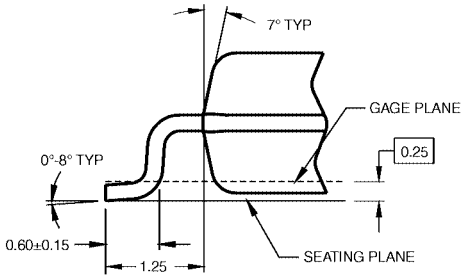
NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

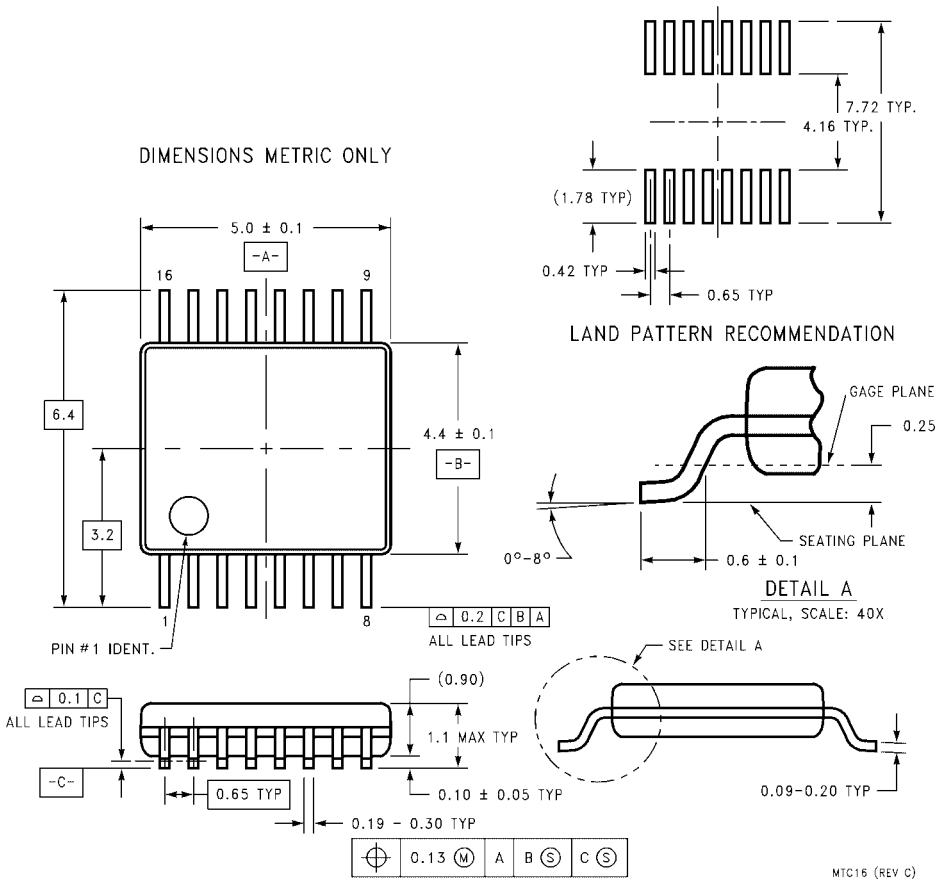
M16DRevB1



DETAIL A

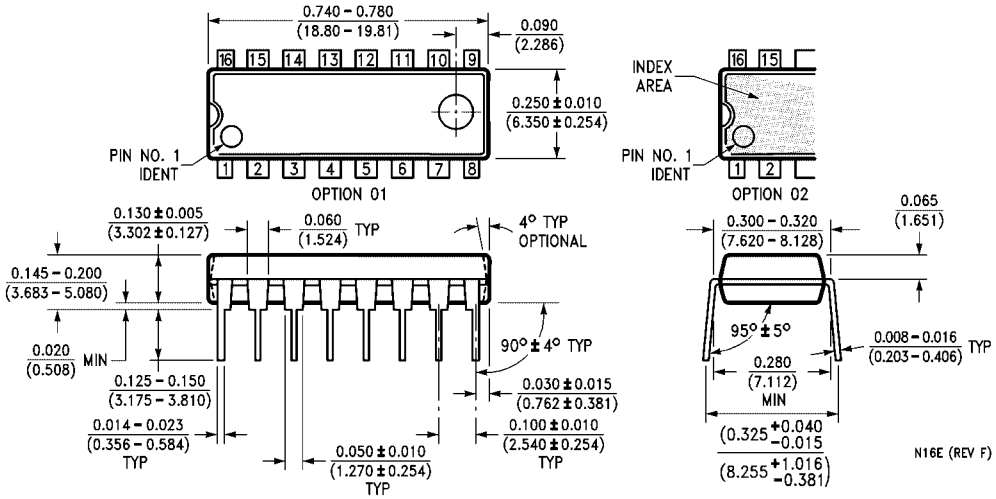
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC175 • 74ACT175
Quad D-Type Flip-Flop

General Description

The AC/ACT175 is a high-speed quad D-type flip-flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D-type inputs is stored during the LOW-to-HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D-type inputs, when LOW.

Features

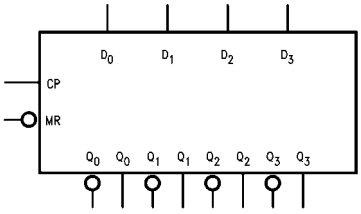
- I_{CC} reduced by 50%
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Asynchronous common reset
- True and complement output
- Outputs source/sink 24 mA
- ACT175 has TTL-compatible inputs

Ordering Code:

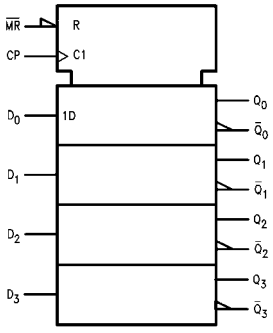
Order Number	Package Number	Package Description
74AC175SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC175SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC175MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC175PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT175SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT175SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT175MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT175PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

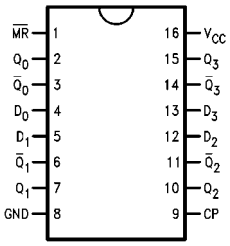
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_3	Data Inputs
CP	Clock Pulse Input
$\overline{MR}$	Master Reset Input
Q_0–Q_3	True Outputs
$\overline{Q}_0$–$\overline{Q}_3$	Complement Outputs

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Functional Description

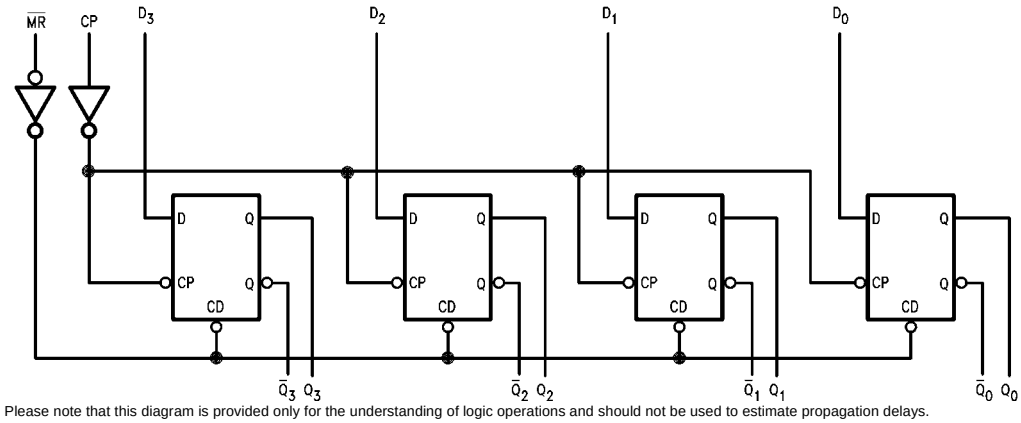
The AC/ACT175 consists of four edge-triggered D-type flip-flops with individual D inputs and Q and $\overline{Q}$ outputs. The Clock and Master Reset are common. The four flip-flops will store the state of their individual D inputs on the LOW-to-HIGH clock (CP) transition, causing individual Q and $\overline{Q}$ outputs to follow. A LOW input on the Master Reset ($\overline{MR}$) will force all Q outputs LOW and $\overline{Q}$ outputs HIGH independent of Clock or Data inputs. The AC/ACT175 is useful for general logic applications where a common Master Reset and Clock are acceptable.

Truth Table

Inputs	Outputs	
@ t_n, $\overline{MR}$ = H	@ t_{n+1}	
D_n	Q_n	$\overline{Q}_n$
L	L	H
H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
t_n = Bit Time before Clock Pulse
t_{n+1} = Bit Time after Clock Pulse

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	2.0	2.0		or $V_{CC} - 0.1V$
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	0.8	0.8		or $V_{CC} - 0.1V$
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
	Output Voltage	5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
	Output Voltage	5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	± 1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current(Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$
	Supply Current						or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
		(Note 7)	Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock	3.3	149	214		139		MHz
	Frequency	5.0	187	244		187		
t_{PLH}	Propagation Delay	3.3	2.0	9.5	12.0	2.0	13.5	ns
	CP to Q_n or $\overline{Q}_n$	5.0	1.5	7.0	9.0	1.0	9.5	
t_{PHL}	Propagation Delay	3.3	2.5	8.5	13.0	2.0	14.5	ns
	CP to Q_n or $\overline{Q}_n$	5.0	1.5	6.0	9.5	1.5	10.5	
t_{PLH}	Propagation Delay	3.3	3.0	7.5	12.5	2.5	13.5	ns
	$\overline{MR}$ to $\overline{Q}_n$	5.0	2.0	5.5	9.0	1.5	10.0	
t_{PHL}	Propagation Delay	3.3	3.0	8.5	11.0	2.5	12.5	ns
	$\overline{MR}$ to Q_n	5.0	2.0	6.0	8.5	1.5	9.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	2.0	4.5	4.5	ns
	D_n to CP	5.0	1.0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	1.0	1.0	1.0	ns
	D_n to CP	5.0	1.0	1.0	1.0	
t_W	CP Pulse Width	3.3	2.5	4.5	4.5	ns
	HIGH or LOW	5.0	2.0	3.5	3.5	
t_W	$\overline{MR}$ Pulse Width, LOW	3.3	2.5	4.5	5.0	ns
		5.0	2.0	3.5	3.5	
t_{REC}	Recovery Time	3.3	−2.0	0	0	ns
	$\overline{MR}$ to CP	5.0	−1.0	0	0	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	175	236		145		MHz
t_{PLH}	Propagation Delay CP to Q_n or $\overline{Q}_n$	5.0	2.0	6.0	10.0	1.5	11.0	ns
t_{PHL}	Propagation Delay CP to Q_n or $\overline{Q}_n$	5.0	2.0	7.0	11.0	1.5	12.0	ns
t_{PLH}	Propagation Delay $\overline{MR}$ to $\overline{Q}_n$	5.0	2.0	6.0	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	2.0	5.5	9.5	1.5	10.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

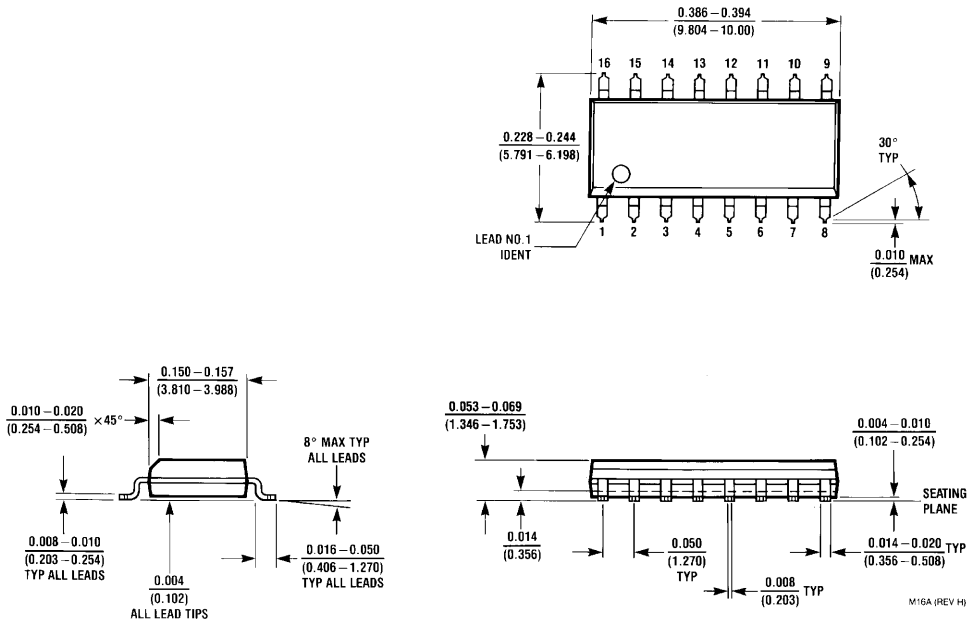
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Typ	Guaranteed Minimum		
t_S (H)	Setup Time	5.0	3.0	2.0	2.0	ns
t_S (L)	D_n to CP		3.0	2.5	2.5	
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	1.0	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	4.0	3.0	3.5	ns
t_W	$\overline{MR}$ Pulse Width, LOW	5.0	4.0	3.0	4.0	ns
t_{rec}	Recovery Time, $\overline{MR}$ to CP	5.0	0	0	0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

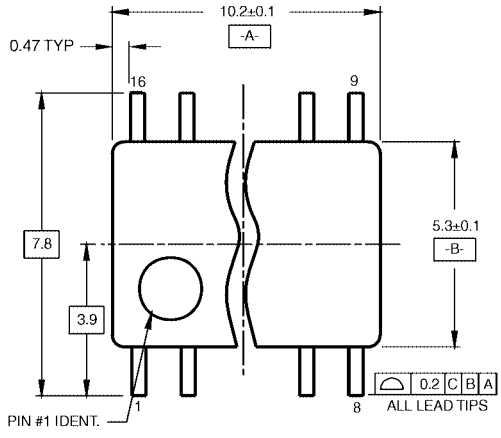
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

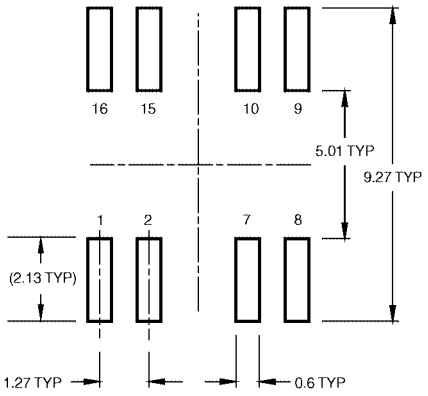
Physical Dimensions inches (millimeters) unless otherwise noted



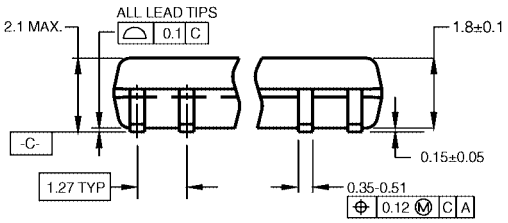
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M16A

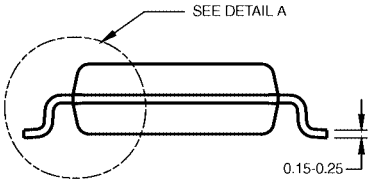
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



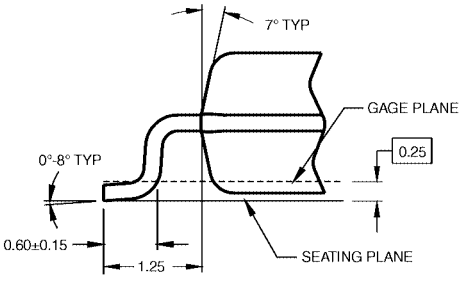


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

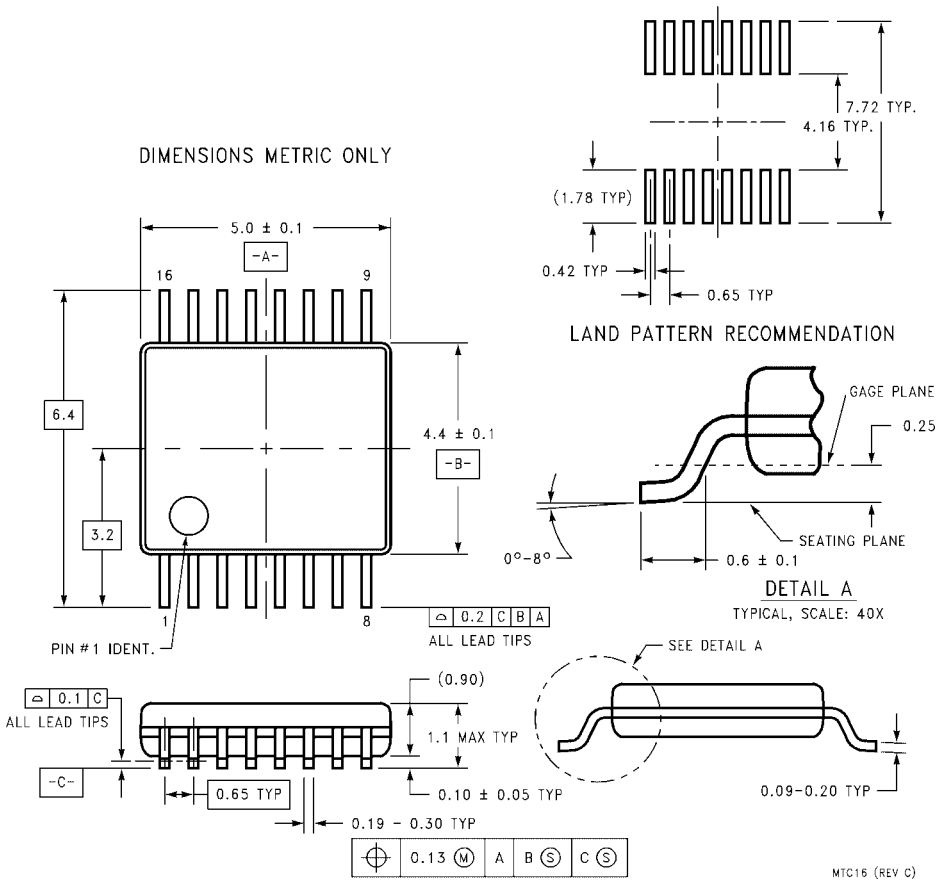
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

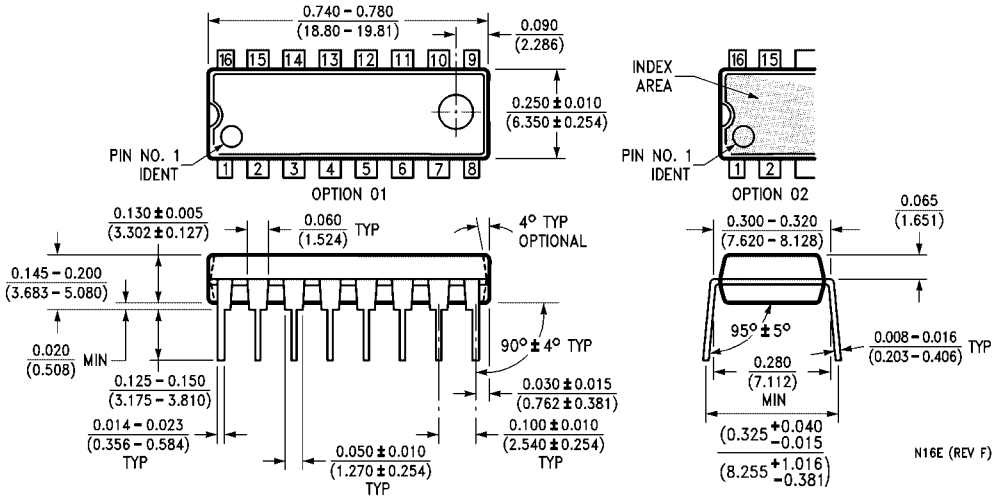
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC191
Up/Down Counter with Preset and Ripple Clock

General Description

The AC191 is a reversible modulo 16 binary counter. It features synchronous counting and asynchronous presetting. The preset feature allows the AC191 to be used in programmable dividers. The Count Enable input, the Terminal Count output and the Ripple Clock output make possible a variety of methods of implementing multistage counters. In the counting modes, state changes are initiated by the rising edge of the clock.

Features

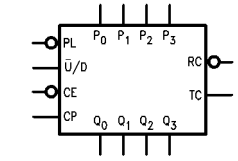
- I_{CC} reduced by 50%
- High speed—133 MHz typical count frequency
- Synchronous counting
- Asynchronous parallel load
- Cascadable
- Outputs source/sink 24 mA

Ordering Code:

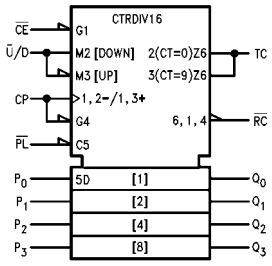
Order Number	Package Number	Package Description
74AC191SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC191SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC191MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC191PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

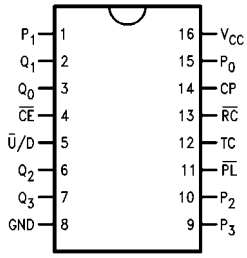
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{CE}$	Count Enable Input
CP	Clock Pulse Input
P_0–P_3	Parallel Data Inputs
$\overline{PL}$	Asynchronous Parallel Load Input
$\overline{U}$ /D	Up/Down Count Control Input
Q_0–Q_3	Flip-Flop Outputs
$\overline{RC}$	Ripple Clock Output
TC	Terminal Count Output

FACT™ is a trademark of Fairchild Semiconductor Corporation.

$\overline{RC}$ Truth Table

Inputs				Outputs
$\overline{PL}$	$\overline{CE}$	TC (Note 1)	CP	$\overline{RC}$
H	L	H	⊓	⊓
H	H	X	X	H
H	X	L	X	H
L	X	X	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition
⊓ = Clock Pulse

Note 1: TC is generated internally

Functional Description

The AC191 is a synchronous up/down counter. The AC191 is organized as a 4-bit binary counter. It contains four edge-triggered flip-flops with internal gating and steering logic to provide individual preset, count-up and count-down operations.

Each circuit has an asynchronous parallel load capability permitting the counter to be preset to any desired number. When the Parallel Load ($\overline{PL}$) input is LOW, information present on the Parallel Load inputs (P_0–P_3) is loaded into the counter and appears on the Q outputs. This operation overrides the counting functions, as indicated in the Mode Select Table.

A HIGH signal on the $\overline{CE}$ input inhibits counting. When $\overline{CE}$ is LOW, internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The direction of counting is determined by the $\overline{U}$/D input signal, as indicated in the Mode Select Table. $\overline{CE}$ and $\overline{U}$/D can be changed with the clock in either state, provided only that the recommended setup and hold times are observed.

Two types of outputs are provided as overflow/underflow indicators. The terminal count (TC) output is normally LOW. It goes HIGH when the circuits reach zero in the count down mode or 15 in the count up mode. The TC output will then remain HIGH until a state change occurs, whether by counting or presetting or until $\overline{U}$/D is changed. The TC output should not be used as a clock signal because it is subject to decoding spikes.

The TC signal is also used internally to enable the Ripple Clock ($\overline{RC}$) output. The $\overline{RC}$ output is normally HIGH. When $\overline{CE}$ is LOW and TC is HIGH, $\overline{RC}$ output will go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again. This feature simplifies the design of multistage counters, as indicated in Figure 1 and Figure 2. In Figure 1, each $\overline{RC}$ output is used as the clock input for the next higher stage. This configuration is particularly advantageous when the clock source has a limited drive capability, since it drives only the first stage. To prevent counting in all stages it is only necessary to inhibit the first stage, since a HIGH signal on $\overline{CE}$ inhibits the $\overline{RC}$ output pulse, as indicated in the $\overline{RC}$ Truth Table. A disadvantage of this configuration, in some applications, is the timing skew between state changes in the first and last stages. This represents the cumulative delay of the clock as it ripples through the preceding stages.

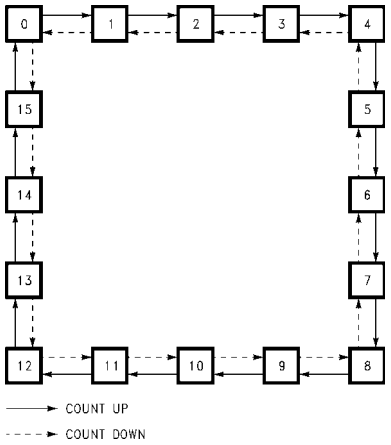
A method of causing state changes to occur simultaneously in all stages is shown in Figure 2. All clock inputs are driven in parallel and the $\overline{RC}$ outputs propagate the carry/borrow signals in ripple fashion. In this configuration the LOW state duration of the clock must be long enough to allow the negative-going edge of the carry/borrow signal to ripple through to the last stage before the clock goes HIGH. There is no such restriction on the HIGH state duration of the clock, since the $\overline{RC}$ output of any device goes HIGH shortly after its CP input goes HIGH.

The configuration shown in Figure 3 avoids ripple delays and their associated restrictions. The $\overline{CE}$ input for a given stage is formed by combining the TC signals from all the preceding stages. Note that in order to inhibit counting an enable signal must be included in each carry gate. The simple inhibit scheme of Figure 1 and Figure 2 doesn't apply, because the TC output of a given stage is not affected by its own $\overline{CE}$.

Mode Select Table

Inputs				Mode
$\overline{PL}$	$\overline{CE}$	$\overline{U}$/D	CP	
H	L	L	⌐	Count Up
H	L	H	⌐	Count Down
L	X	X	X	Preset (Asyn.)
H	H	X	X	No Change (Hold)

State Diagram



Functional Description (continued)

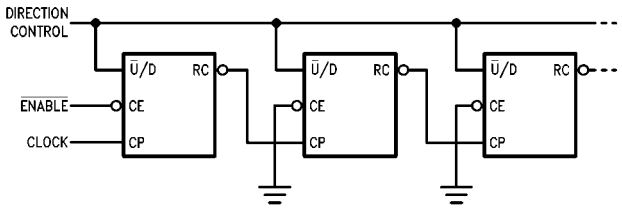


FIGURE 1. N-Stage Counter Using Ripple Clock

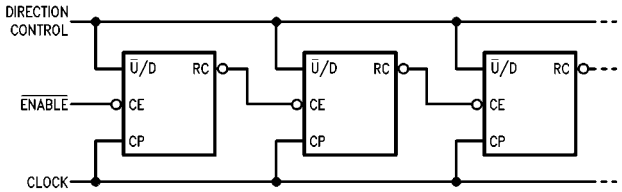


FIGURE 2. Synchronous N-Stage Counter Using Ripple Carry/Borrow

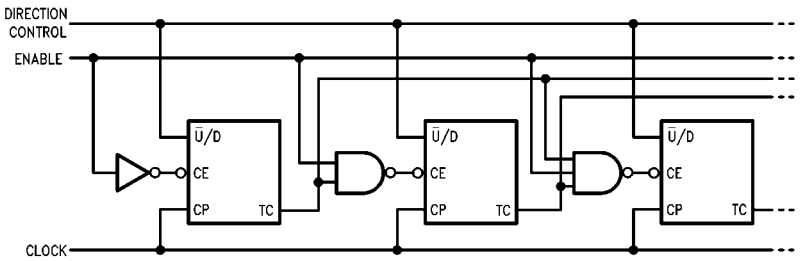
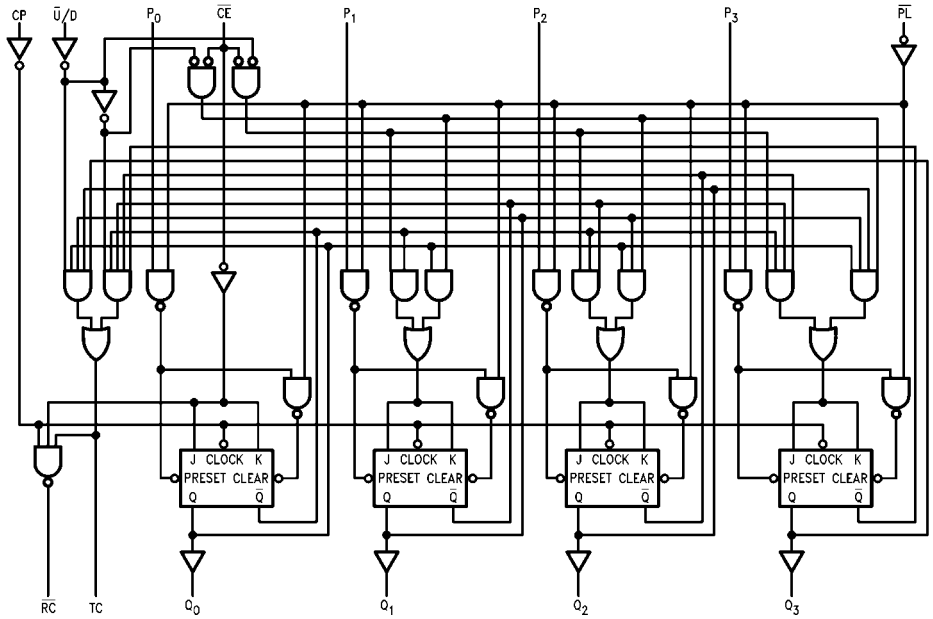


FIGURE 3. Synchronous N-Stage Counter with Parallel Gated Carry/Borrow

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		3.0		2.56	2.46		V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} −12 mA
		5.5		4.86	4.76		I_{OH} = −24 mA
							I_{OH},= −24 mA (Note 3)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		3.0		0.36	0.44		V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 12 mA
		5.5		0.36	0.44		I_{OL} = 24 mA
							I_{OL} = 24 mA (Note 3)
I_{IN} (Note 5)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 5)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 6)	C_L = 50 pF, T_A = +25°C			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Count	3.3	70	105		65		MHz
	Frequency	5.0	90	133		85		
t_{PLH}	Propagation Delay	3.3	2.0	8.5	15.0	1.5	16.0	ns
	CP to Q_n	5.0	1.5	6.0	11.0	1.5	12.0	
t_{PHL}	Propagation Delay	3.3	2.5	8.5	14.5	2.0	16.0	ns
	CP to Q_n	5.0	1.5	6.0	10.5	1.5	11.5	
t_{PLH}	Propagation Delay	3.3	3.5	10.5	18.0	2.5	20.0	ns
	CP to TC	5.0	2.5	7.5	12.0	1.5	14.0	
t_{PHL}	Propagation Delay	3.3	4.0	10.5	17.5	3.0	19.0	ns
	CP to TC	5.0	2.5	7.5	12.5	2.0	13.5	
t_{PLH}	Propagation Delay	3.3	2.5	7.5	12.0	2.0	13.5	ns
	CP to $\overline{RC}$	5.0	2.0	5.5	9.5	1.0	10.5	
t_{PHL}	Propagation Delay	3.3	2.5	7.0	11.5	2.0	12.5	ns
	CP to $\overline{RC}$	5.0	1.5	5.0	8.5	1.0	9.5	
t_{PLH}	Propagation Delay	3.3	2.5	7.0	12.0	1.5	13.5	ns
	$\overline{CE}$ to $\overline{RC}$	5.0	1.5	5.0	8.5	1.0	9.5	
t_{PHL}	Propagation Delay	3.3	2.0	6.5	11.0	1.5	12.5	ns
	$\overline{CE}$ to $\overline{RC}$	5.0	1.5	5.0	8.0	1.0	9.0	
t_{PLH}	Propagation Delay	3.3	2.5	6.5	12.5	2.0	14.5	ns
	$\overline{U}$ /D to $\overline{RC}$	5.0	1.5	5.0	9.0	1.0	10.0	
t_{PHL}	Propagation Delay	3.3	2.5	7.0	12.0	2.0	13.5	ns
	$\overline{U}$ /D to $\overline{RC}$	5.0	1.5	5.0	8.5	1.0	10.0	
t_{PLH}	Propagation Delay	3.3	2.0	7.0	11.5	1.5	13.5	ns
	$\overline{U}$ /D to TC	5.0	1.5	5.0	8.5	1.0	9.5	
t_{PHL}	Propagation Delay	3.3	2.0	6.5	11.0	1.5	12.5	ns
	$\overline{U}$ /D to TC	5.0	1.5	5.0	8.5	1.0	9.5	
t_{PLH}	Propagation Delay	3.3	2.5	8.0	13.5	2.0	15.5	ns
	P_n to Q_n	5.0	2.0	5.5	9.5	1.0	10.5	
t_{PHL}	Propagation Delay	3.3	2.5	7.5	13.0	1.5	14.5	ns
	P_n to Q_n	5.0	1.5	5.5	9.5	1.0	10.5	
t_{PLH}	Propagation Delay	3.3	3.5	9.5	14.5	2.5	17.5	ns
	$\overline{PL}$ to Q_n	5.0	2.0	5.5	9.5	1.0	10.5	
t_{PHL}	Propagation Delay	3.3	3.0	8.0	13.5	2.0	15.5	ns
	$\overline{PL}$ to Q_n	5.0	2.0	6.0	10.0	1.5	11.0	

Note 6: Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements

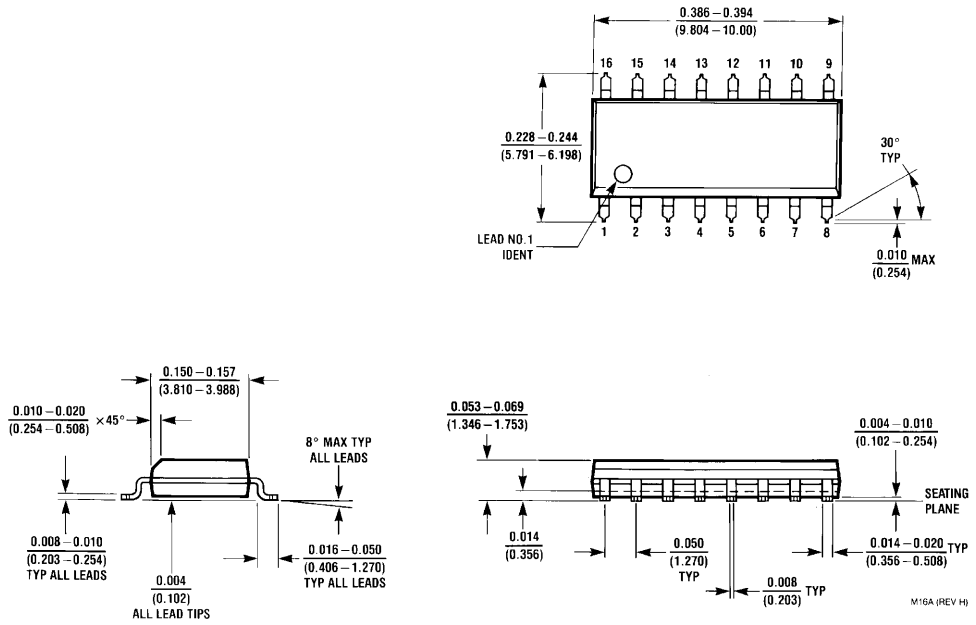
Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	1.0	3.0	3.0	ns
	P_n to $\overline{PL}$	5.0	0.5	2.0	2.5	
t_H	Hold Time, HIGH or LOW	3.3	−1.5	0.5	1.0	ns
	P_n to $\overline{PL}$	5.0	−0.5	1.0	1.0	
t_S	Setup Time, LOW	3.3	3.0	6.0	7.0	ns
	$\overline{CE}$ to CP	5.0	1.5	4.0	4.5	
t_H	Hold Time, LOW	3.3	−4.0	−0.5	−0.5	ns
	$\overline{CE}$ to CP	5.0	−2.5	0	0	
t_S	Setup Time, HIGH or LOW	3.3	4.0	8.0	9.0	ns
	$\overline{U}$/D to CP	5.0	2.5	5.5	6.5	
t_H	Hold Time, HIGH or LOW	3.3	−5.0	0	0	ns
	$\overline{U}$/D to CP	5.0	−3.0	0.5	0.5	
t_W	$\overline{PL}$ Pulse Width, LOW	3.3	2.0	3.5	4.0	ns
		5.0	1.0	1.0	1.0	
t_W	CP Pulse Width, LOW	3.3	2.0	3.5	4.0	ns
		5.0	2.0	3.0	4.0	
t_{rec}	Recovery Time	3.3	−0.5	0	0	ns
	$\overline{PL}$ to CP	5.0	−1.0	0	0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

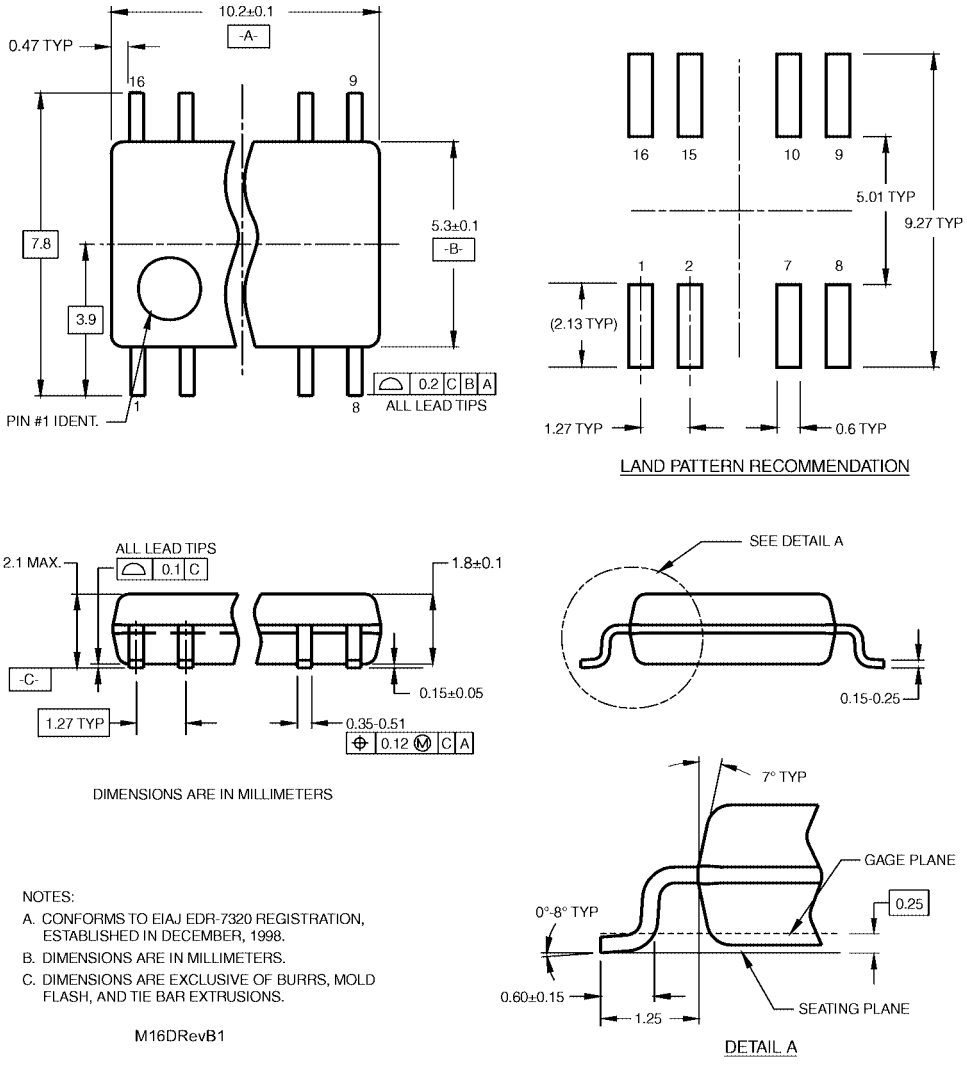
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	75.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

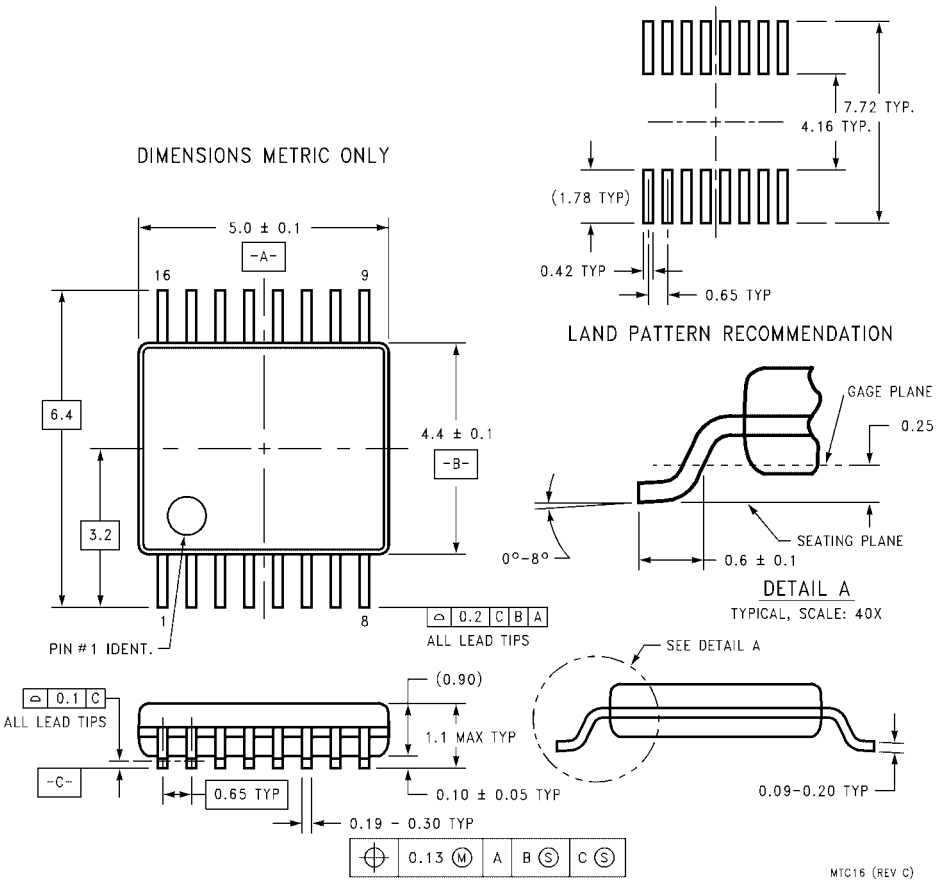
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

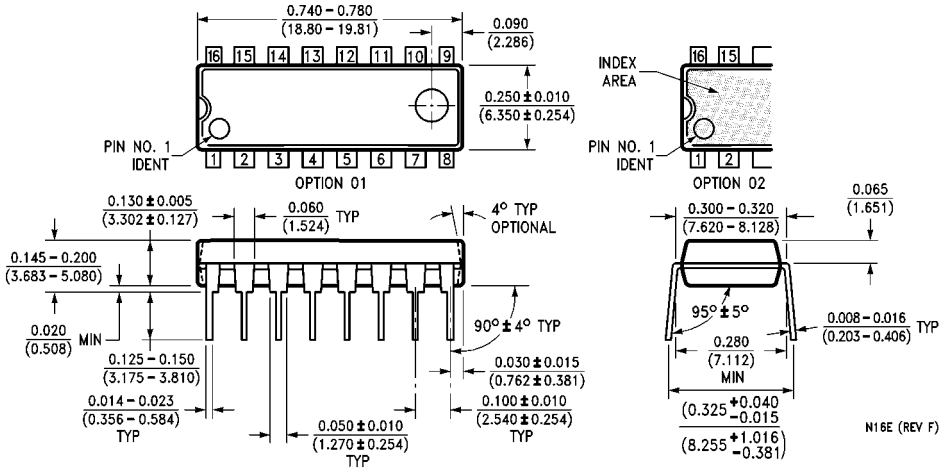
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC20
Dual 4-Input NAND Gate

General Description

The AC20 contains four 4-input NAND gates.

Features

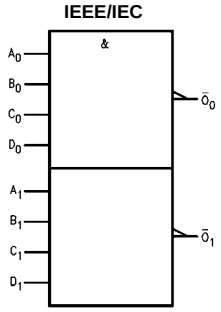
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA

Ordering Code:

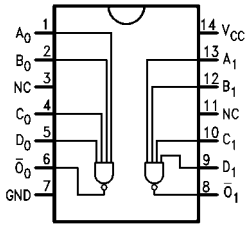
Order Number	Package Number	Package Description
74AC20SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC20SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC20MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC20PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n, C_n, D_n	Inputs
$\overline{O}_n$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

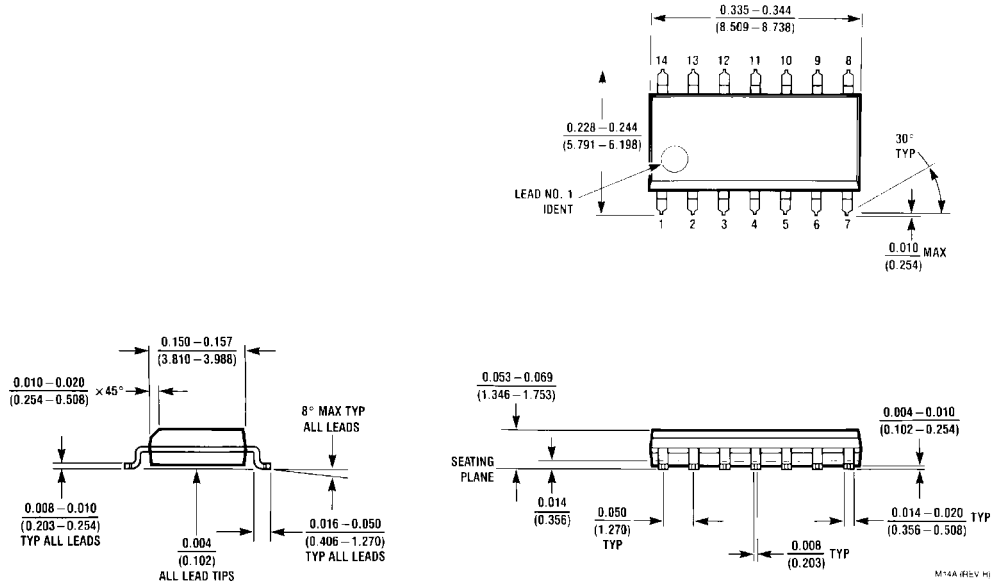
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	2.0	6.0	8.5	1.5	10.0	ns
		5.0	1.5	5.0	7.0	1.0	8.0	
t_{PHL}	Propagation Delay	3.3	1.5	5.0	7.0	1.0	9.0	ns
		5.0	1.5	4.0	6.0	1.0	7.0	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

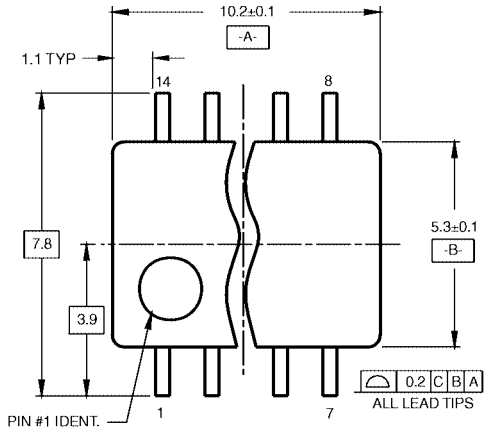
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

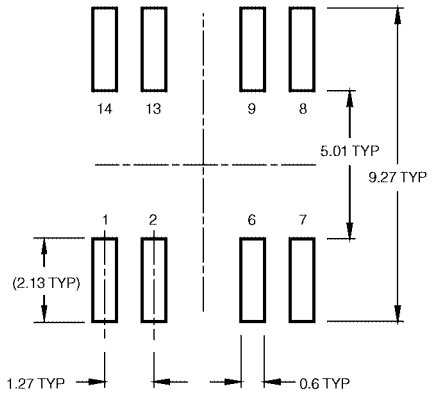
Physical Dimensions inches (millimeters) unless otherwise noted



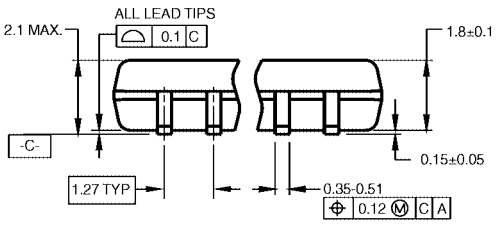
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number M14A

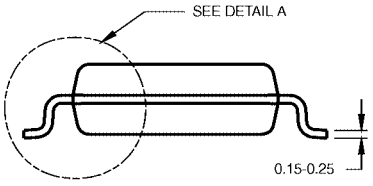
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



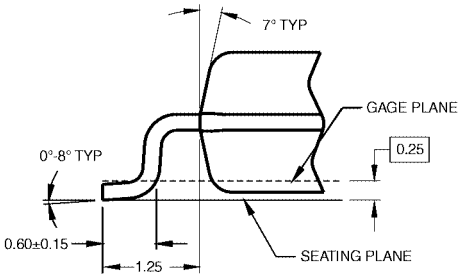


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

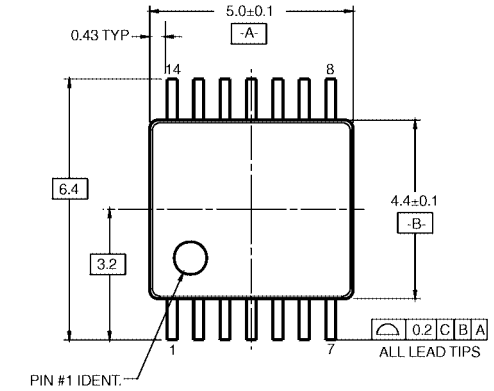
B. DIMENSIONS ARE IN MILLIMETERS.

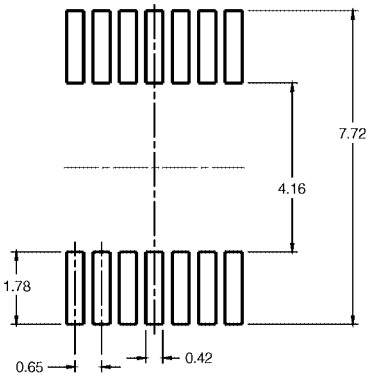
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

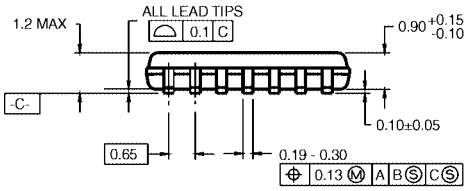
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

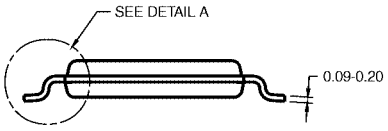
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

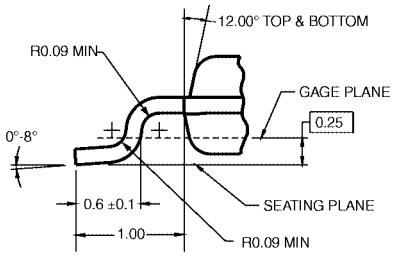




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

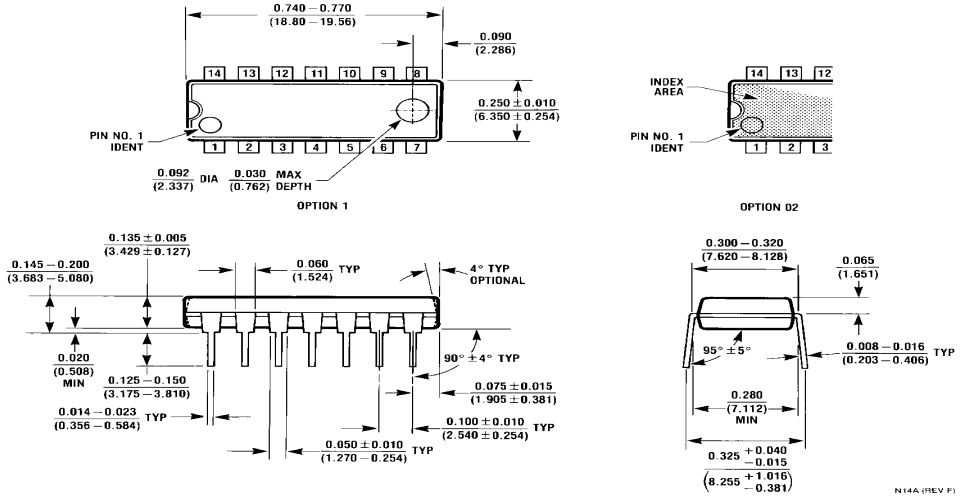
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC240 • 74ACT240
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The AC/ACT240 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

- I_{CC} and I_{OZ} reduced by 50%
- Inverting 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- ACT240 has TTL-compatible inputs

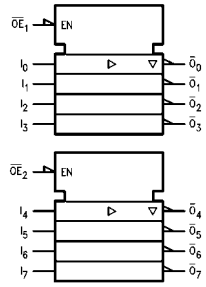
Ordering Code:

Order Number	Package Number	Package Description
74AC240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153,4.4mm Wide
74AC240PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153,4.4mm Wide
74ACT240PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

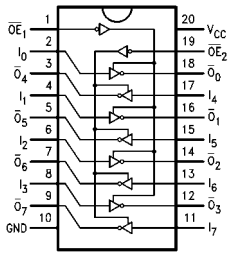
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices V_{IN} from 30% to 70% of V_{CC} V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices V_{IN} from 0.8V to 2.0V V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	6.0	8.0	1.0	9.0	ns
	Data to Output	5.0	1.5	4.5	6.5	1.0	7.0	
t_{PHL}	Propagation Delay	3.3	1.5	5.5	8.0	1.0	8.5	ns
	Data to Output	5.0	1.5	4.5	6.0	1.0	6.5	
t_{PZH}	Output Enable Time	3.3	1.5	6.0	10.5	1.0	11.0	ns
		5.0	1.5	5.0	7.0	1.0	8.0	
t_{PZL}	Output Enable Time	3.3	1.5	7.0	10.0	1.0	11.0	ns
		5.0	1.5	5.5	8.0	1.0	8.5	
t_{PHZ}	Output Disable Time	3.3	1.5	7.0	10.0	1.0	10.5	ns
		5.0	1.5	6.5	9.0	1.0	9.5	
t_{PLZ}	Output Disable Time	3.3	1.5	7.5	10.5	1.0	11.5	ns
		5.0	1.5	6.5	9.0	1.0	9.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics

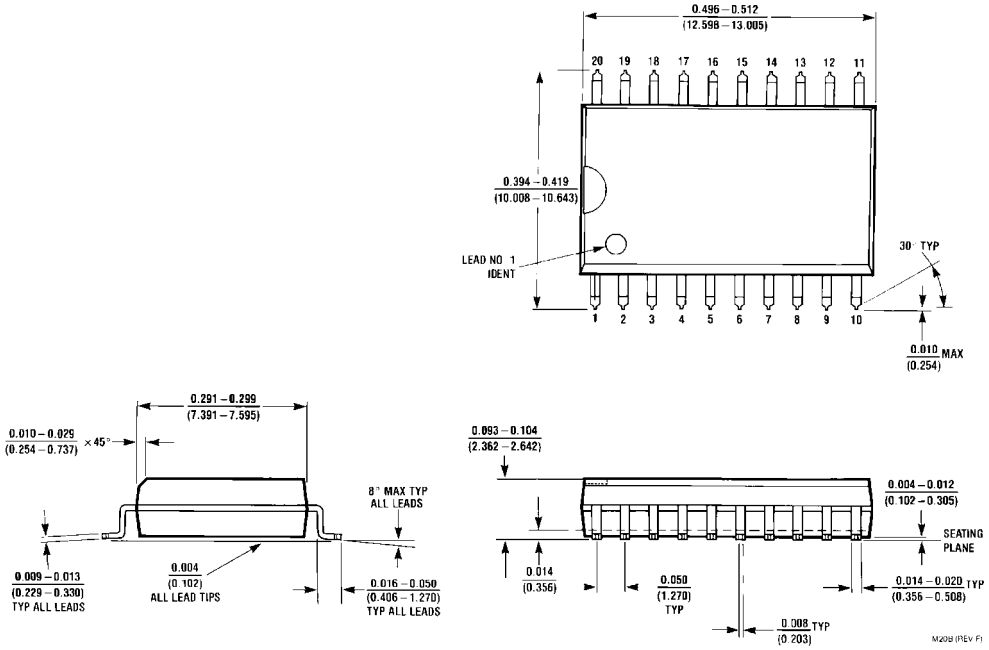
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	1.5	6.0	8.5	1.5	9.5	ns
t_{PHL}	Propagation Delay Data to Output	5.0	1.5	5.5	7.5	1.5	8.5	ns
t_{PZH}	Output Enable Time	5.0	1.5	7.0	8.5	1.0	9.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	7.0	9.5	1.5	10.5	ns
t_{PHZ}	Output Disable Time	5.0	2.0	8.0	9.5	2.0	10.5	ns
t_{PLZ}	Output Disable Time	5.0	2.5	6.5	10.0	2.0	10.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

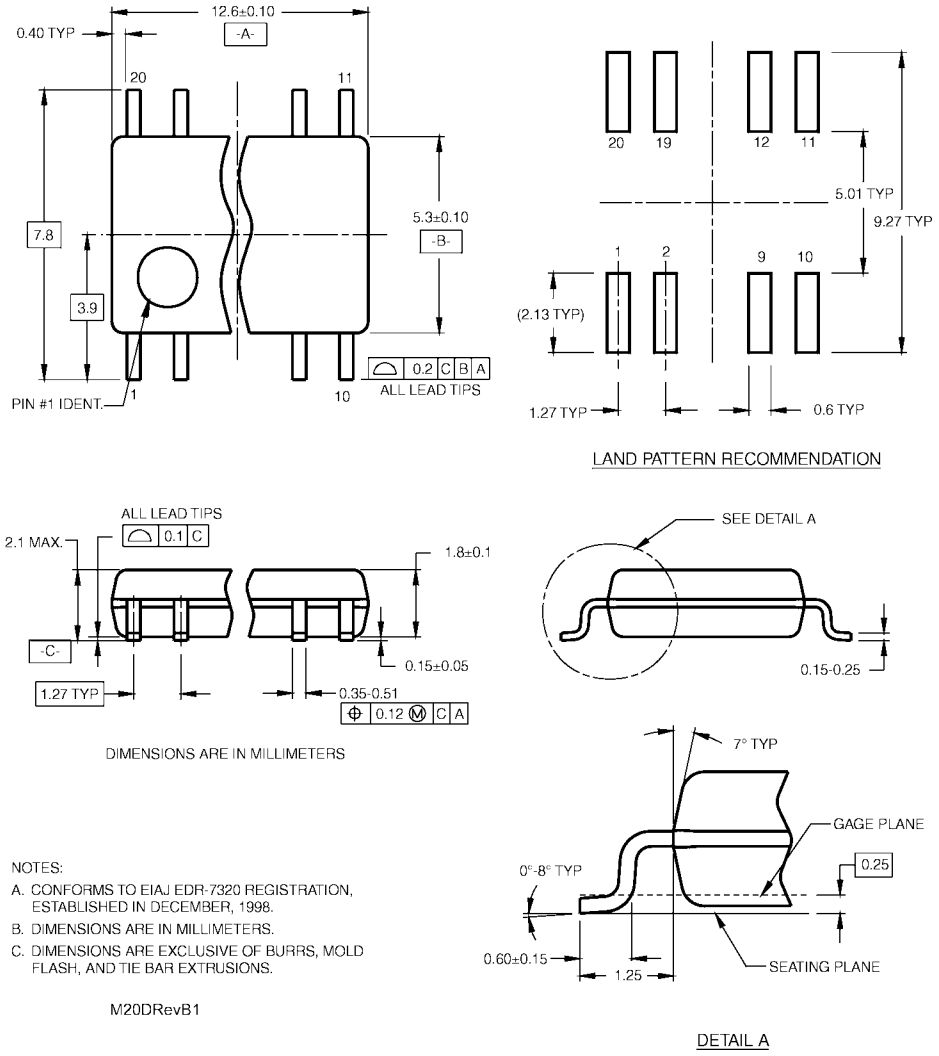
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

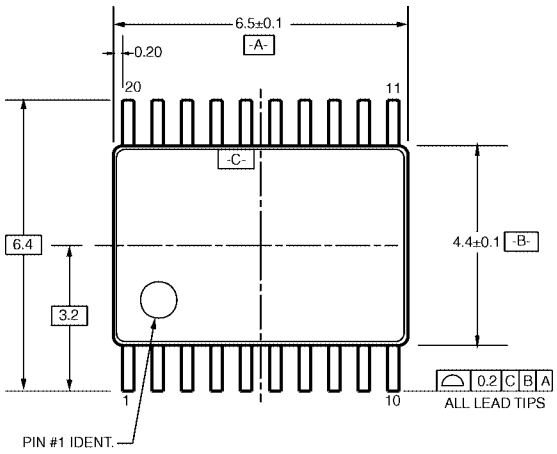
B. DIMENSIONS ARE IN MILLIMETERS.

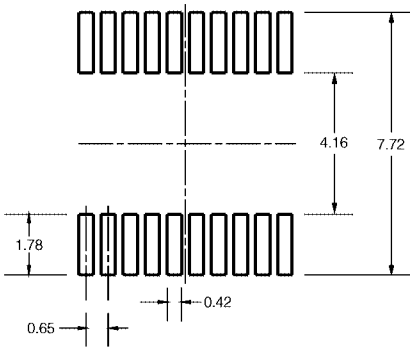
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

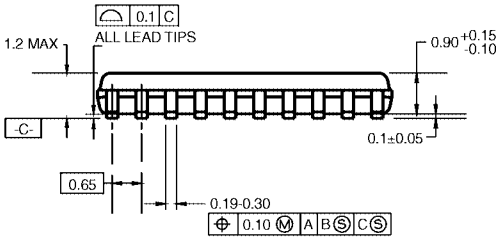
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

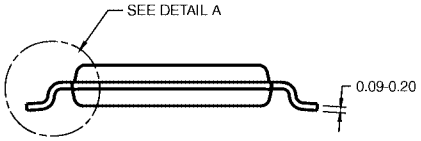
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

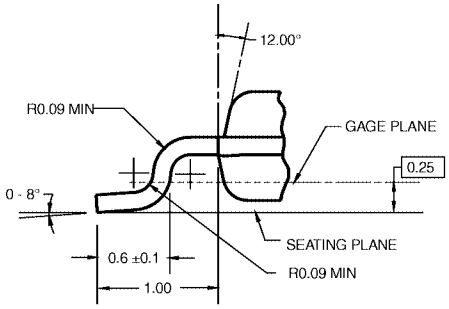
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

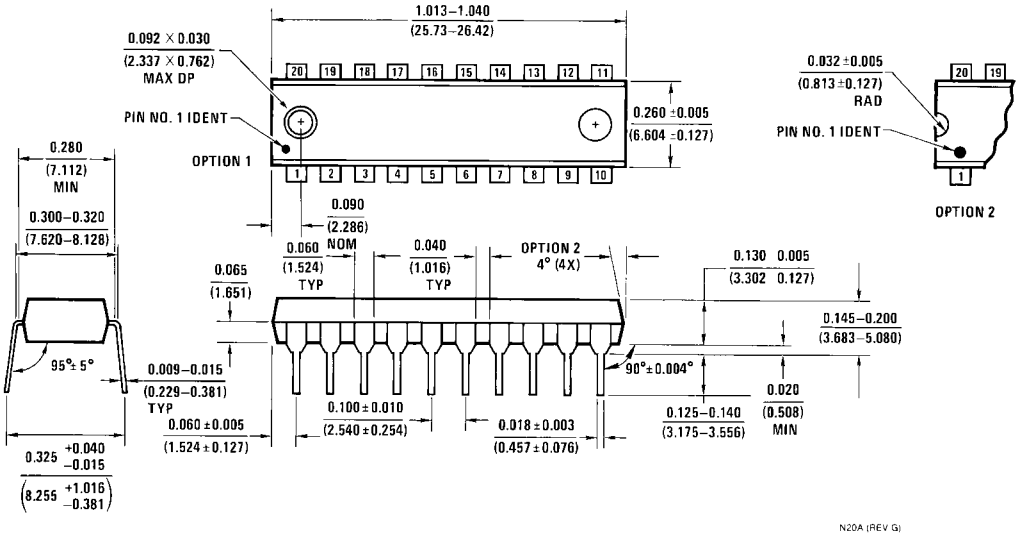
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC241 • 74ACT241
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The AC/ACT241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus-oriented transmitter or receiver which provides improved PC board density.

Features

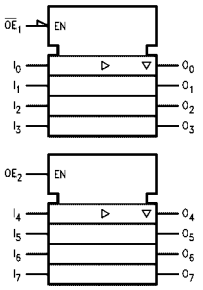
- I_{CC} and I_{OZ} reduced by 50%
- Non-inverting 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- ACT241 has TTL-compatible inputs

Ordering Code:

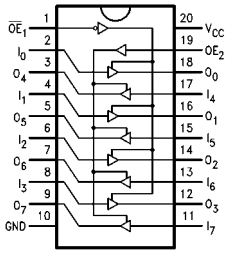
Order Number	Package Number	Package Description
74AC241SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC241SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC241MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC241PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT241SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT241SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT241MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT241PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also avialable in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$	3-STATE Output Enable Input
OE_2	3-STATE Output Enable Input (Active HIGH)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
OE_2	I_n	(Pins 3, 5, 7, 9)
H	L	L
H	H	H
L	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}(V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_N (Note 4)	Maximum Input Leakage Currentt	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.25	± 2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay Data to Output	3.3	1.5	6.0	9.0	1.5	10.0	ns
		5.0	1.5	5.0	7.0	1.0	7.5	
t_{PHL}	Propagation Delay Data to Output	3.3	1.5	6.0	9.0	1.0	10.5	ns
		5.0	1.5	4.5	7.0	1.0	7.5	
t_{PZH}	Output Enable Time	3.3	1.5	6.5	12.5	1.0	13.0	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t_{PZL}	Output Enable Time	3.3	1.5	7.0	12.0	1.5	13.0	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t_{PHZ}	Output Disable Time	3.3	2.0	8.0	12.0	2.0	12.5	ns
		5.0	1.5	6.5	10.0	1.0	10.5	
t_{PLZ}	Output Disable Time	3.3	1.5	7.0	12.5	1.0	13.0	ns
		5.0	1.5	6.0	10.0	1.0	10.5	

Note 7: Voltage Range 3.3 is 3.3V ± 3.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

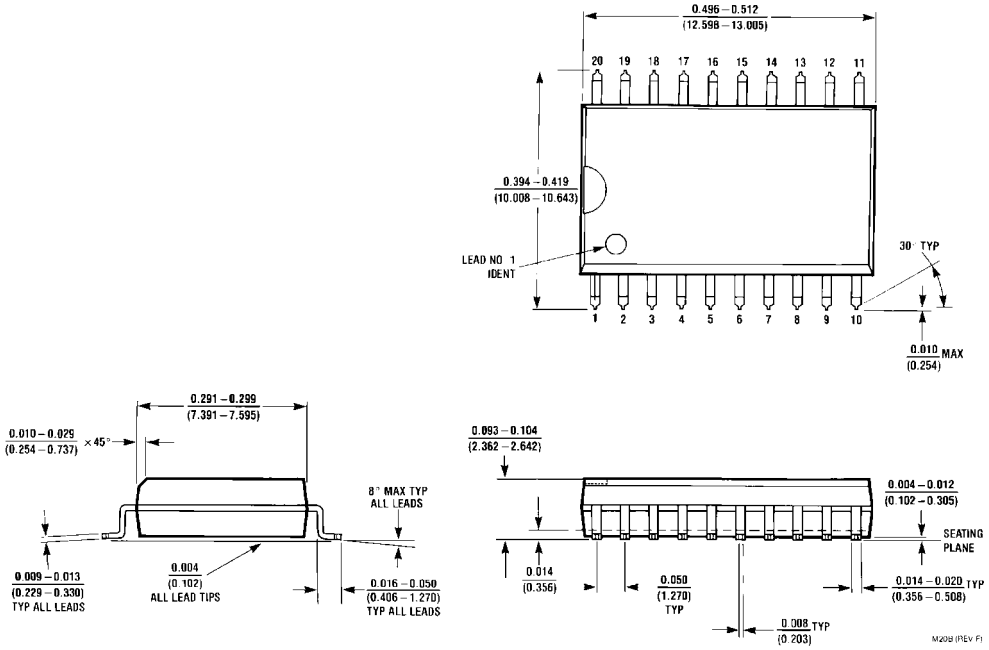
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	1.5	6.5	9.0	1.5	10.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	1.5	7.0	9.0	1.5	10.0	ns
t_{PZH}	Output Enable Time	5.0	1.5	6.0	9.0	1.0	10.0	ns
t_{PZL}	Output Enable Time	5.0	1.5	7.0	10.0	1.5	11.0	ns
t_{PHZ}	Output Disable Time	5.0	1.5	8.0	10.5	1.5	11.5	ns
t_{PLZ}	Output Disable Time	5.0	2.0	7.0	10.5	1.5	11.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

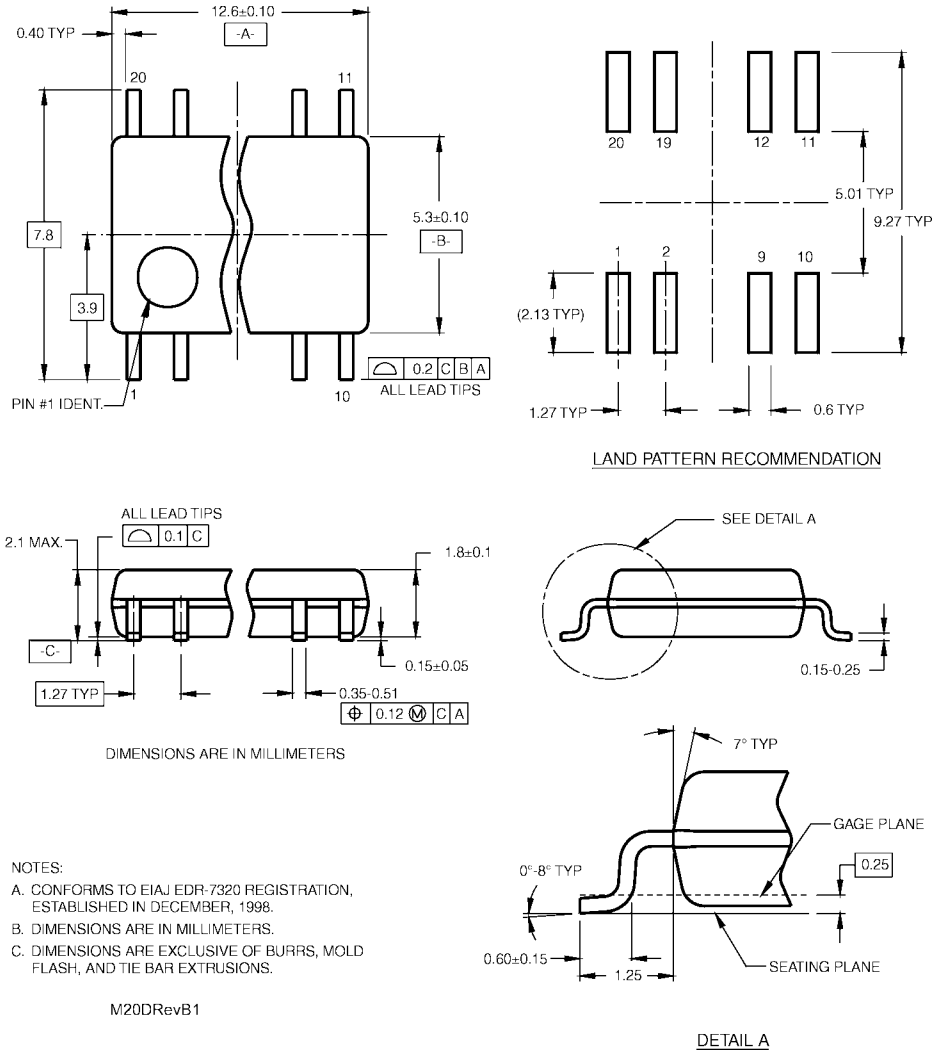
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

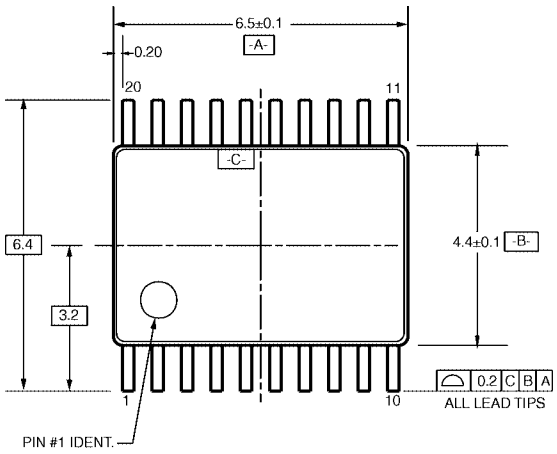
B. DIMENSIONS ARE IN MILLIMETERS.

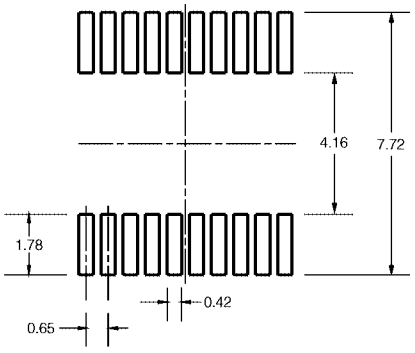
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

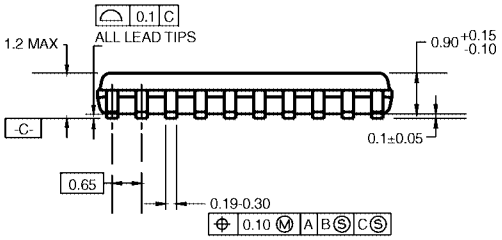
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

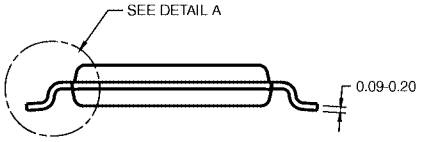
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

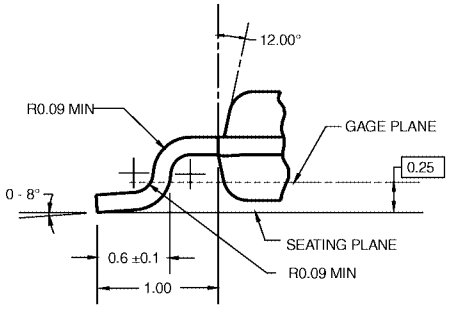
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

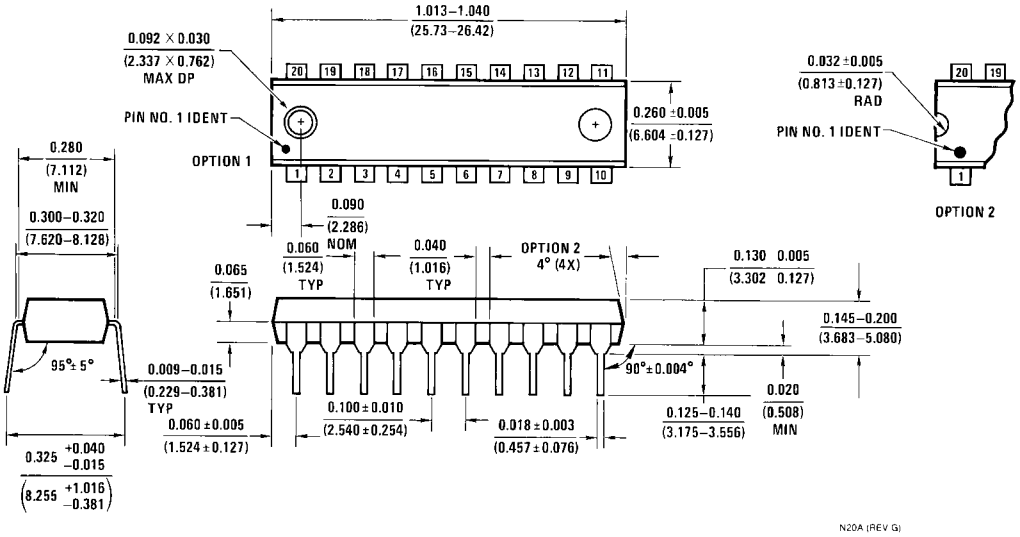
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC244 • 74ACT244
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The AC/ACT244 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus-oriented transmitter/receiver which provides improved PC board density.

Features

- I_{CC} and I_{OZ} reduced by 50%
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- ACT244 has TTL-compatible inputs

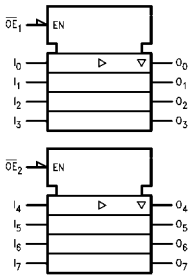
Ordering Code:

Order Number	Package Number	Package Description
74AC244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACT244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

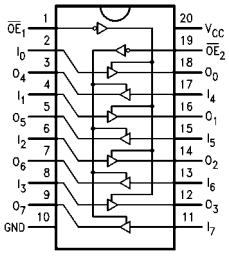
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



FACT™ is a trademark of Fairchild Semiconductor Corporation.

Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −55°C to +125°C Guaranteed Limits	T_A = −40°C to +85°C Guaranteed Limits	Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4	5.4		
		3.0		2.56	2.4	2.46		I_{OH} = 12 mA
		4.5		3.86	3.7	3.76	V	I_{OH} = 24 mA
		5.5		4.86	4.7	4.76		I_{OH} = 24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1	0.1		
		3.0		0.36	0.50	0.44		I_{OL} = 12 mA
		4.5		0.36	0.50	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.50	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±5.0	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, V_{GND} V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			50	75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−50	−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	80.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -55°C$ to $+125°C$ Guaranteed Limits		$T_A = -40°C$ to $+85°C$ Guaranteed Limits	Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4	5.4		
								$I_{OH} = 12$
		4.5		3.86	3.70	3.76	V	$I_{OH} = 24$ mA
		5.5		4.86	4.70	4.76		$I_{OH} = 24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1	0.1		
								$I_{OL} = 12$ mA
		4.5		0.36	0.50	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.50	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±5.0	±2.5	μA	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.6	1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			50	75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−50	−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	80.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	2.0	6.5	9.0	1.0	12.5	1.5	10.0	ns
	Data to Output	5.0	1.5	5.0	7.0	1.0	9.5	1.0	7.5	
t_{PHL}	Propagation Delay	3.3	2.0	6.5	9.0	1.0	12.0	2.0	10.0	ns
	Data to Output	5.0	1.5	5.0	7.0	1.0	9.0	1.0	7.5	
t_{PZH}	Output Enable Time	3.3	2.0	6.0	10.5	1.0	11.5	1.5	11.0	ns
		5.0	1.5	5.0	7.0	1.0	9.0	1.5	8.0	
t_{PZL}	Output Enable Time	3.3	2.5	7.5	10.0	1.0	13.0	2.0	11.0	ns
		5.0	1.5	5.5	8.0	1.0	10.5	1.5	8.5	
t_{PHZ}	Output Disable Time	3.3	3.0	7.0	10.0	1.0	12.5	1.5	10.5	ns
		5.0	2.5	6.5	9.0	1.0	10.5	1.0	9.5	
t_{PLZ}	Output Disable Time	3.3	2.5	7.5	10.5	1.0	13.0	2.5	11.5	ns
		5.0	2.0	6.5	9.0	1.0	11.0	2.0	9.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

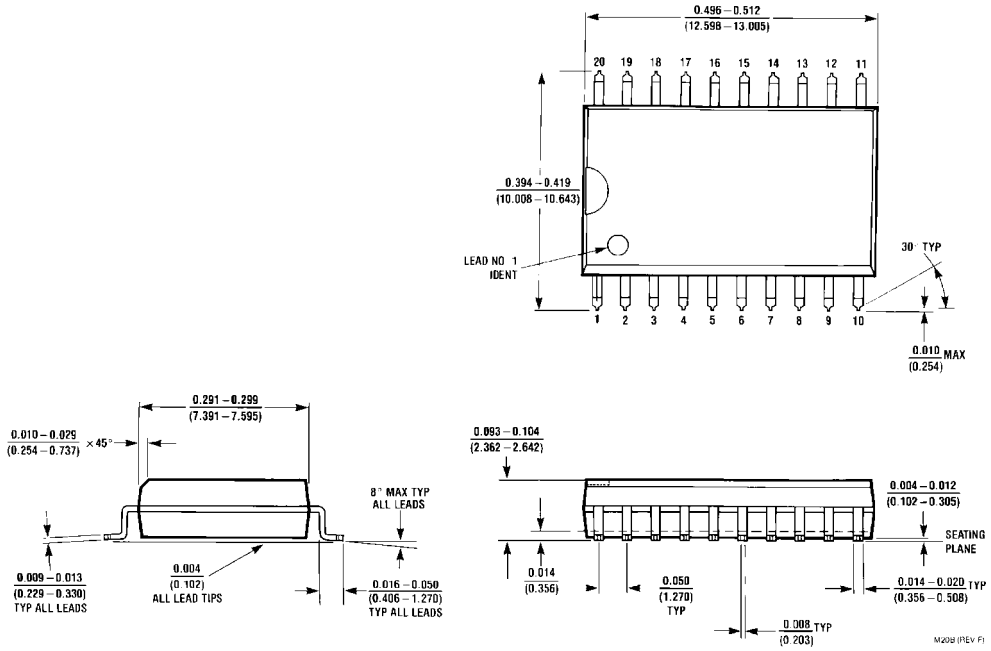
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	2.0	6.5	9.0	1.0	10.0	1.5	10.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	2.0	7.0	9.0	1.0	10.0	1.5	10.0	ns
t_{PZH}	Output Enable Time	5.0	1.5	6.0	8.5	1.0	9.5	1.0	9.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	7.0	9.5	1.0	11.0	1.5	10.5	ns
t_{PHZ}	Output Disable Time	5.0	2.0	7.0	9.5	1.0	11.0	1.5	10.5	ns
t_{PLZ}	Output Disable Time	5.0	2.5	7.5	10.0	1.0	11.5	2.0	10.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

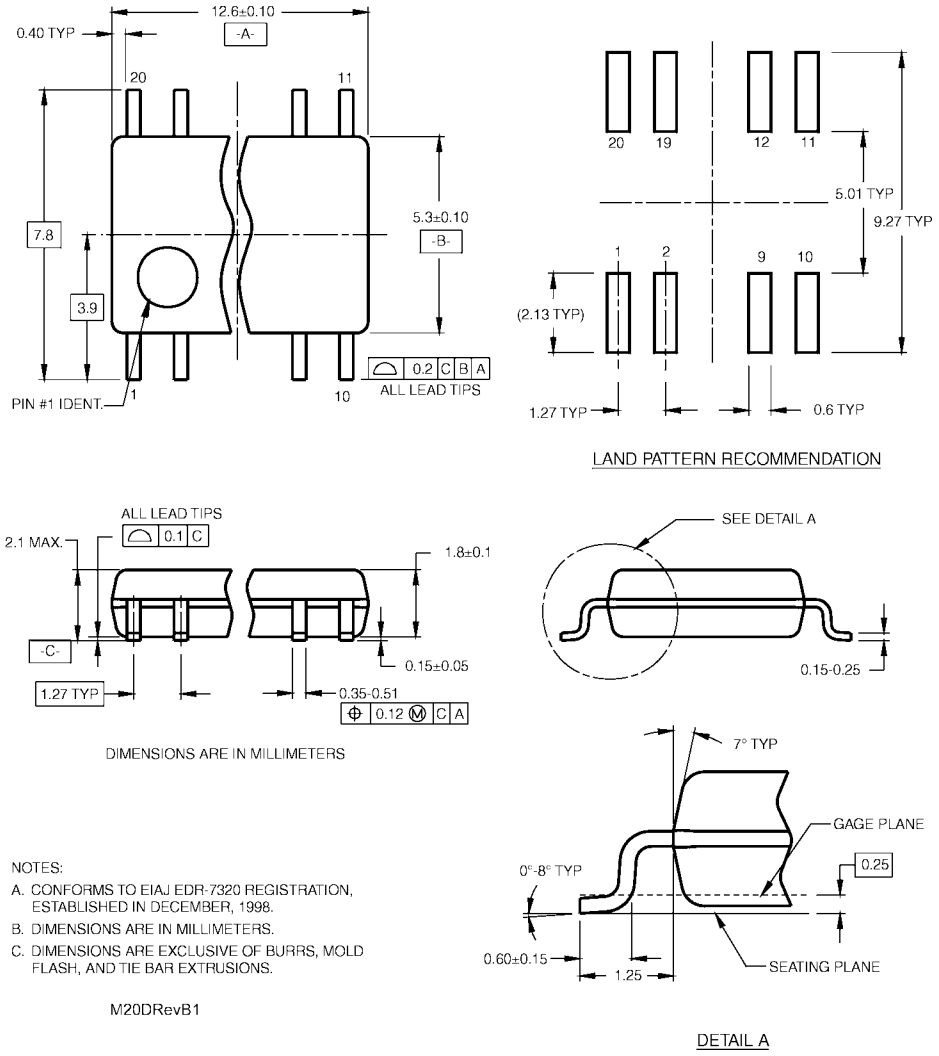
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

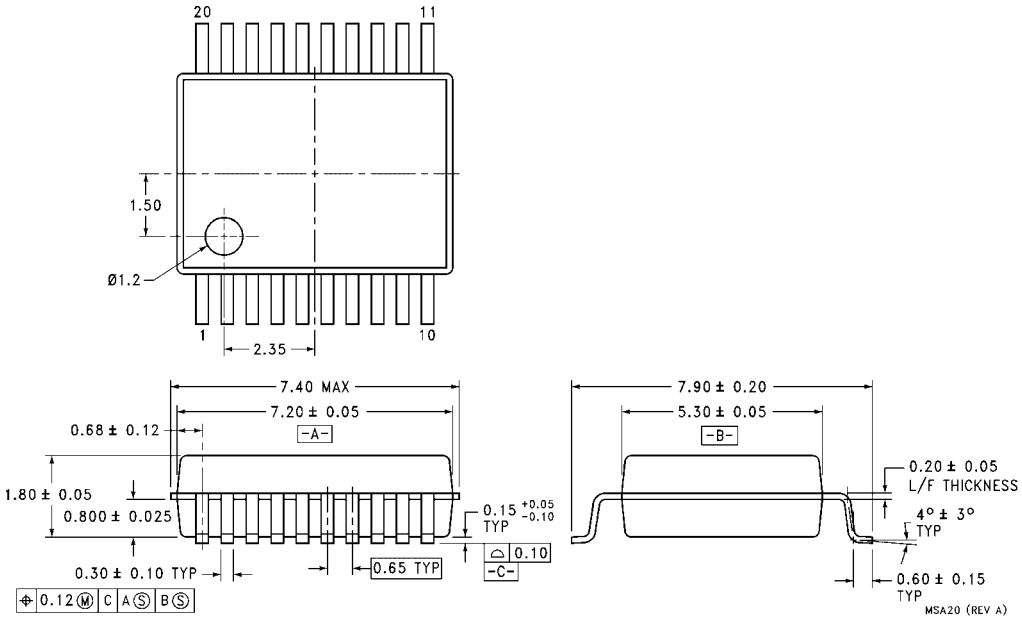
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

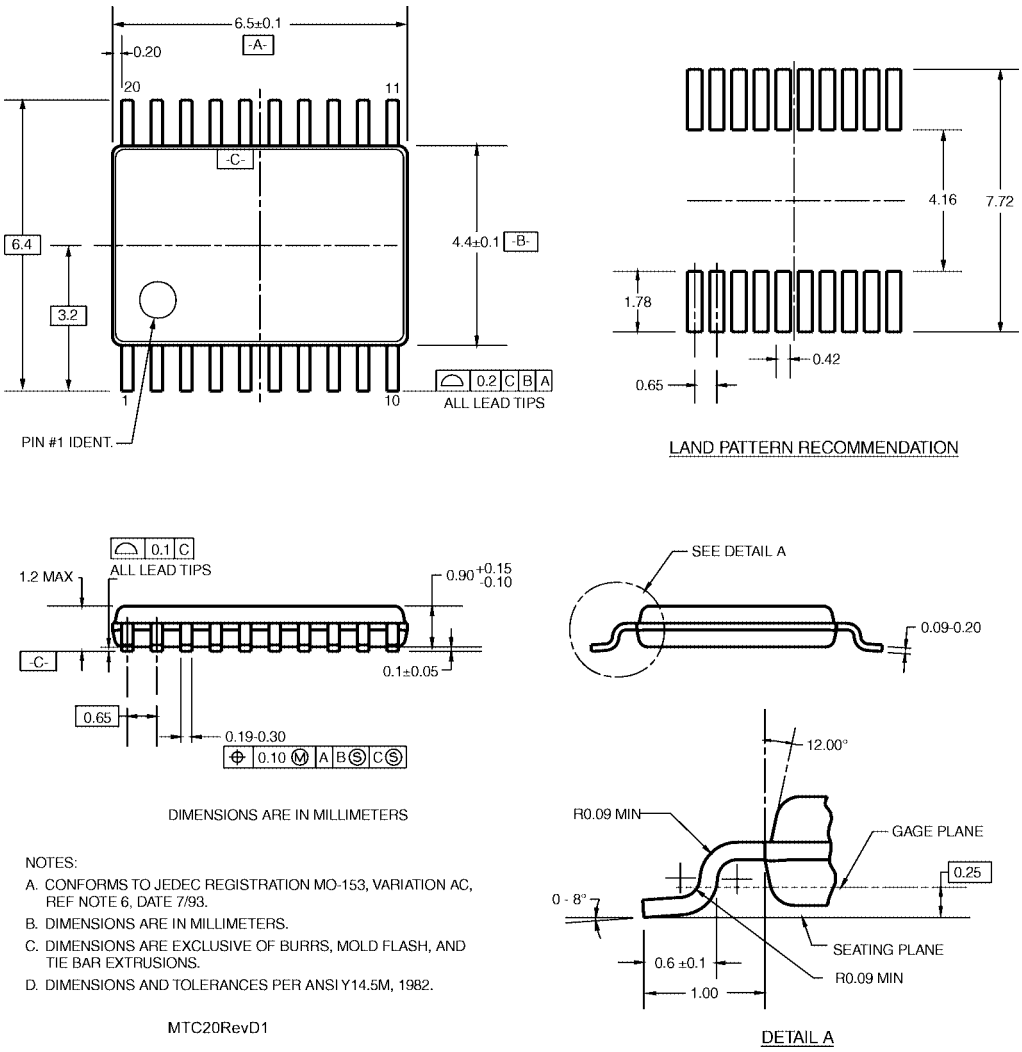
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

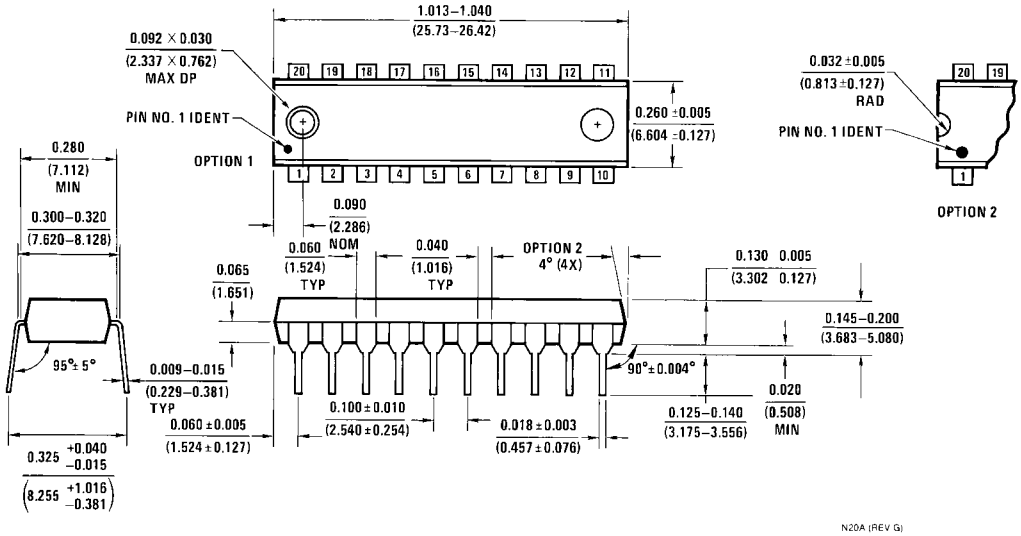
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC245 • 74ACT245
Octal Bidirectional Transceiver with 3-STATE Inputs/Outputs

General Description

The AC/ACT245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at both the A and B ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

Features

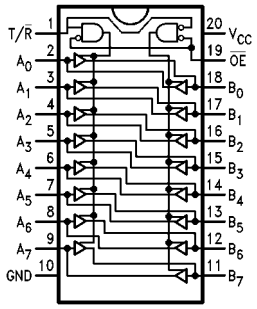
- I_{CC} and I_{OZ} reduced by 50%
- Noninverting buffers
- Bidirectional data path
- A and B outputs source/sink 24 mA
- ACT245 has TTL-compatible inputs

Ordering Code:

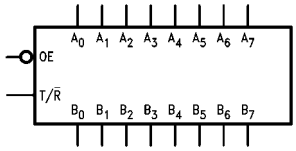
Order Number	Package Number	Package Description
74AC245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74AC245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACT245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACT245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

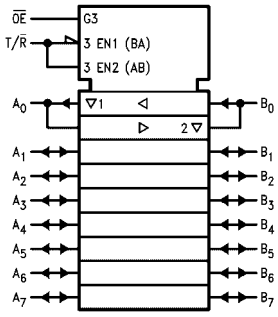
Connection Diagram



Logic Symbols



IEEE/IEC



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A 3-STATE Inputs or 3-STATE Outputs
B_0–B_7	Side B 3-STATE Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Dynamic Output	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Current Minimum (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		± 0.3	± 3.0	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Dynamic Output Current Minimum (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.3	±3.0	μA	V_I (OE) = V_{IL}, V_{IH} $V_I = V_{CC}$, GND $V_O = V_{CC}$, GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay A_n to B_n or B_n to A_n	3.3	1.5	5.0	8.5	1.0	9.0	ns
		5.0	1.5	3.5	6.5	1.0	7.0	
t_{PHL}	Propagation Delay A_n to B_n or B_n to A_n	3.3	1.5	5.0	8.5	1.0	9.0	ns
		5.0	1.5	3.5	6.0	1.0	7.0	
t_{PZH}	Output Enable Time	3.3	2.5	7.0	11.5	2.0	12.5	ns
		5.0	1.5	5.0	8.5	1.0	9.0	
t_{PZL}	Output Enable Time	3.3	2.5	7.5	12.0	2.0	13.5	ns
		5.0	1.5	5.5	9.0	1.0	9.5	
t_{PHZ}	Output Disable Time	3.3	2.0	6.5	12.0	1.0	12.5	ns
		5.0	1.5	5.5	9.0	1.0	10.0	
t_{PLZ}	Output Disable Time	3.3	2.0	7.0	11.5	1.5	13.0	ns
		5.0	1.5	5.5	9.0	1.0	10.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

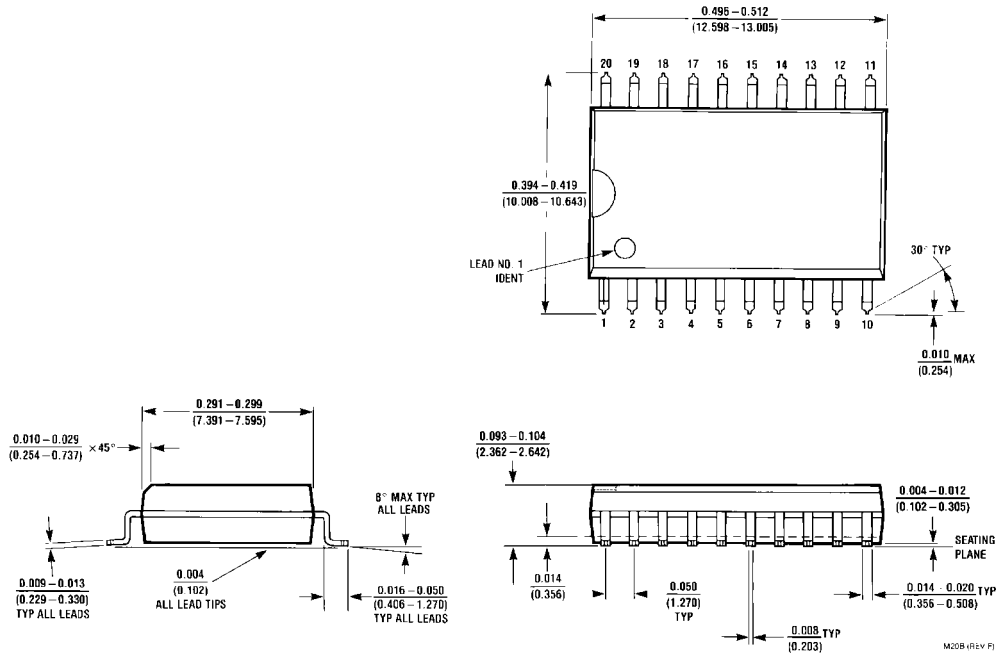
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay A_n to B_n or B_n to A_n	5.0	1.5	4.0	7.5	1.5	8.0	ns
t_{PHL}	Propagation Delay A_n to B_n or B_n to A_n	5.0	1.5	4.0	8.0	1.0	9.0	ns
t_{PZH}	Output Enable Time	5.0	1.5	5.0	10.0	1.5	11.0	ns
t_{PZL}	Output Enable Time	5.0	1.5	5.5	10.0	1.5	12.0	ns
t_{PHZ}	Output Disable Time	5.0	1.5	5.5	10.0	1.0	11.0	ns
t_{PLZ}	Output Disable Time	5.0	2.0	5.0	10.0	1.5	11.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

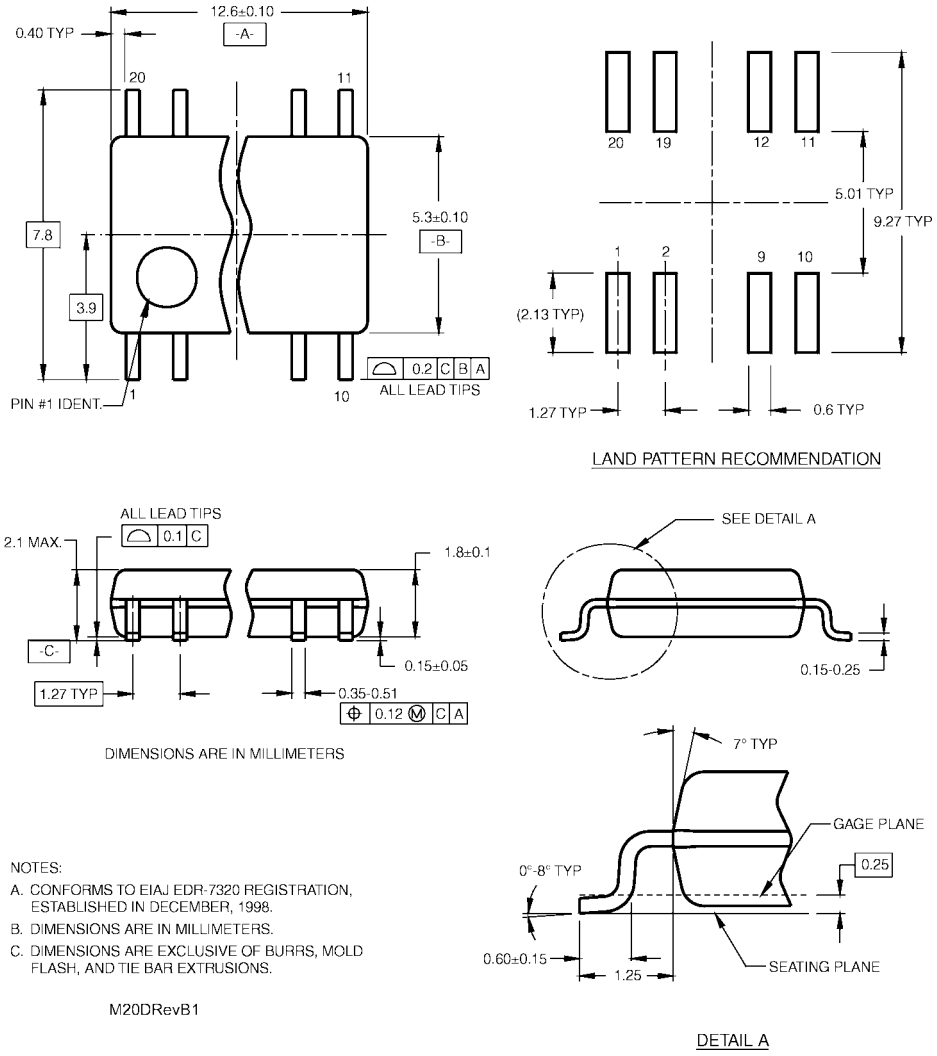
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
$C_{I/O}$	Input/Output Capacitance	15.0	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

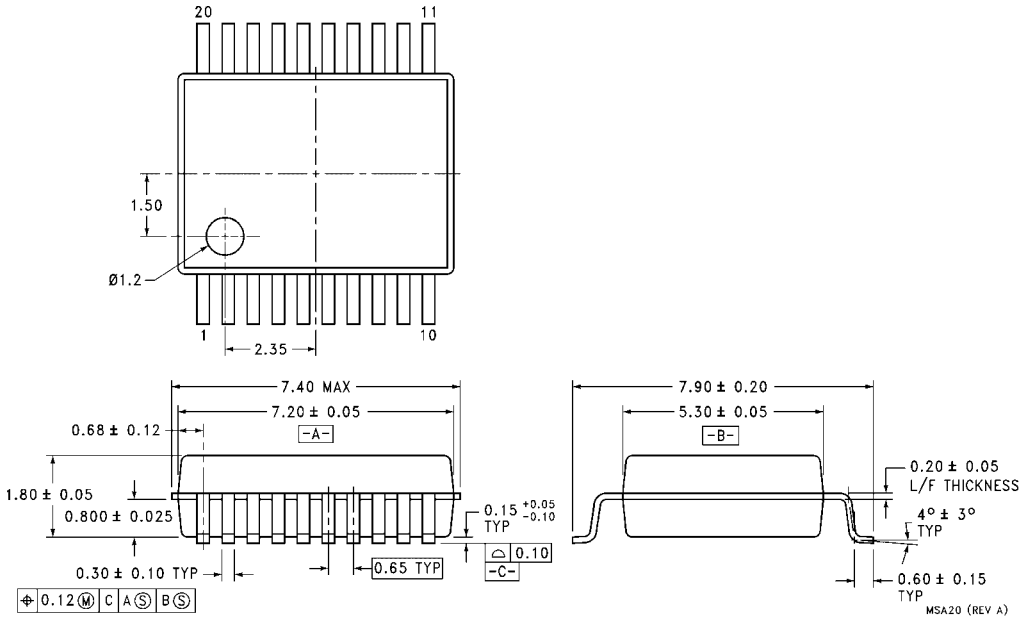
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

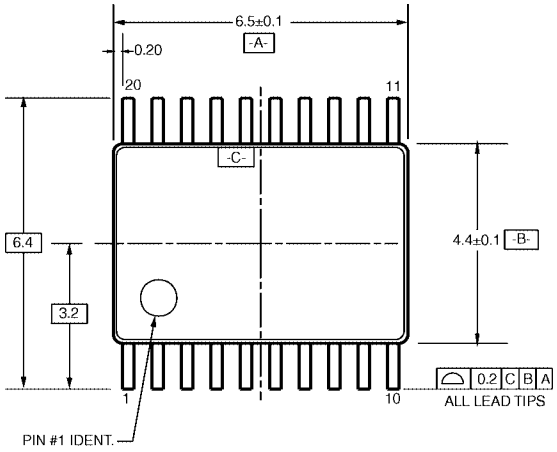
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

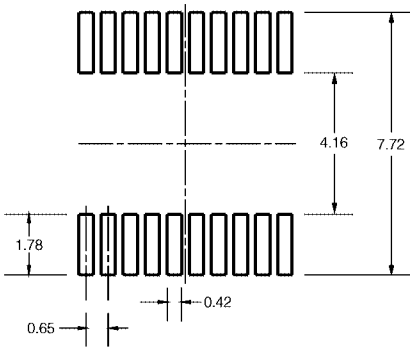
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



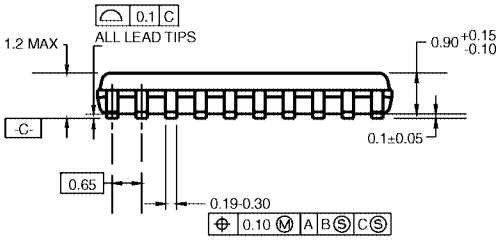
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

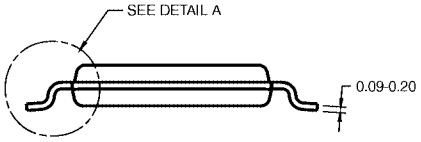
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

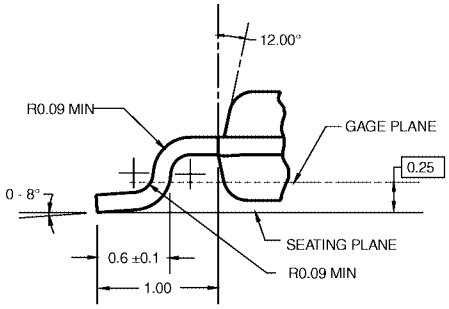
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

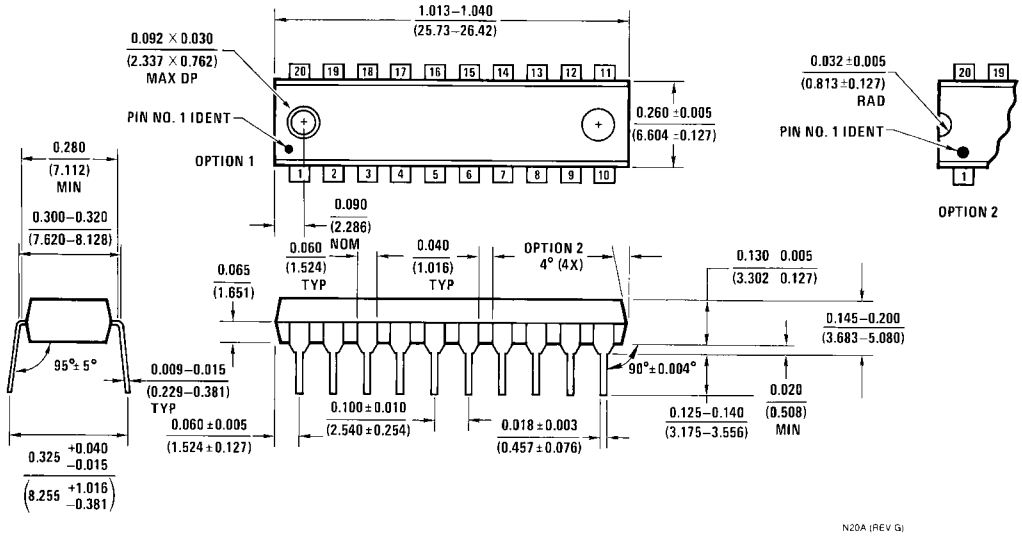
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package, (TSSOP) JEDEC
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC251 • 74ACT251
8-Input Multiplexer with 3-STATE Output

General Description

The AC/ACT251 is a high-speed 8-input digital multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. It can be used as universal function generator to generate any logic function of four variables. Both true and complementary outputs are provided.

Features

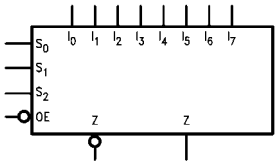
- I_{CC} reduced by 50%
- Multifunctional capability
- On-chip select logic decoding
- Inverting and noninverting 3-STATE outputs
- Outputs source/sink 24 mA
- ACT251 has TTL-compatible inputs

Ordering Code:

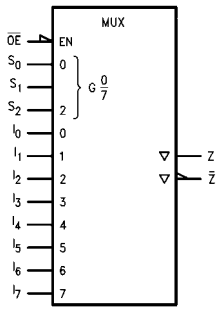
Order Number	Package Number	Package Description
74AC251SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74AC251SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC251MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC251PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT251SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74ACT251MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT251PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

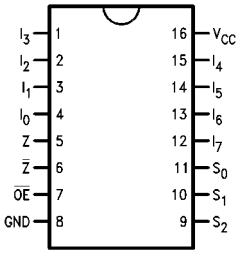
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
S_0–S_2	Select Inputs
$\overline{OE}$	3-STATE Output Enable Input
I_0–I_7	Multiplexer Inputs
Z	3-STATE Multiplexer Output
$\overline{Z}$	Complementary 3-STATE Multiplexer Output

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

This device is a logical implementation of a single-pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0, S_1, S_2. Both true and complementary outputs are provided. The Output Enable input ($\overline{OE}$) is active LOW. When it is activated, the logic function provided at the output is:

$$Z = \overline{OE} \bullet (I_0 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_1 \bullet S_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_2 \bullet \overline{S}_0 \bullet S_1 \bullet \overline{S}_2 + I_3 \bullet S_0 \bullet S_1 \bullet \overline{S}_2 + I_4 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet S_2 + I_5 \bullet S_0 \bullet \overline{S}_1 \bullet S_2 + I_6 \bullet \overline{S}_0 \bullet S_1 \bullet S_2 + I_7 \bullet S_0 \bullet S_1 \bullet S_2)$$

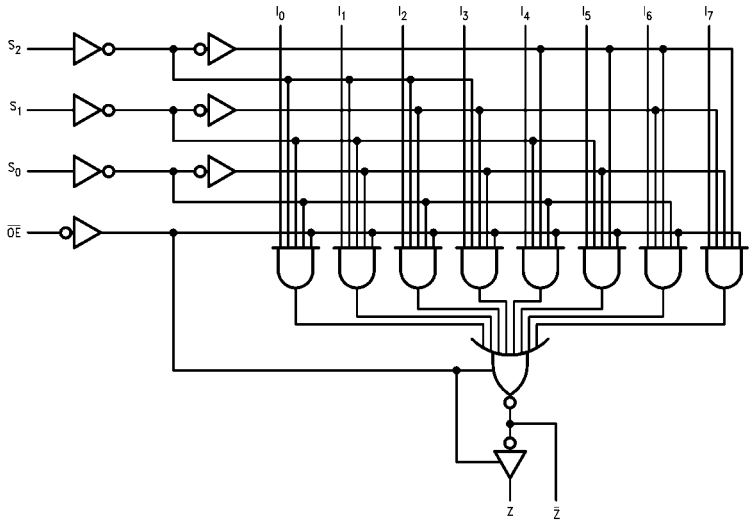
When the Output Enable is HIGH, both outputs are in the high impedance (High Z) state. This feature allows multiplexer expansion by tying the outputs of up to 128 devices together. When the outputs of the 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. The Output Enable signals should be designed to ensure there is no overlap in the active-LOW portion of the enable voltages.

Truth Table

Inputs				Outputs	
$\overline{OE}$	S_2	S_1	S_0	$\overline{Z}$	Z
H	X	X	X	Z	Z
L	L	L	L	$\overline{I}_0$	I_0
L	L	L	H	$\overline{I}_1$	I_1
L	L	H	L	$\overline{I}_2$	I_2
L	L	H	H	$\overline{I}_3$	I_3
L	H	L	L	$\overline{I}_4$	I_4
L	H	L	H	$\overline{I}_5$	I_5
L	H	H	L	$\overline{I}_6$	I_6
L	H	H	H	$\overline{I}_7$	I_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, V_{GND}
							V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Curent	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	μA	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z or $\overline{Z}$	3.3	1.5	11.5	17.5	1.5	19.0	ns
		5.0	1.5	8.5	12.5	1.5	13.5	
t_{PHL}	Propagation Delay S_n to Z or $\overline{Z}$	3.3	1.5	11.0	17.5	1.5	19.0	ns
		5.0	1.5	8.0	12.5	1.5	13.5	
t_{PLH}	Propagation Delay I_n to Z or $\overline{Z}$	3.3	1.5	10.0	14.0	1.5	15.5	ns
		5.0	1.5	7.0	10.0	1.5	11.0	
t_{PHL}	Propagation Delay I_n to Z or $\overline{Z}$	3.3	1.5	9.0	14.0	1.5	15.5	ns
		5.0	1.5	6.5	10.0	1.5	11.0	
t_{PZH}	Output Enable Time $\overline{OE}$ to Z or $\overline{Z}$	3.3	1.5	7.5	11.0	1.5	12.0	ns
		5.0	1.5	5.5	8.0	1.5	9.0	
t_{PZL}	Output Enable Time $\overline{OE}$ to Z or $\overline{Z}$	3.3	1.5	7.5	11.0	1.5	12.0	ns
		5.0	1.5	5.5	8.0	1.5	9.0	
t_{PHZ}	Output Disable Time $\overline{OE}$ to Z or $\overline{Z}$	3.3	1.5	8.5	11.5	1.5	13.0	ns
		5.0	1.5	7.0	9.5	1.5	10.0	
t_{PLZ}	Output Disable Time $\overline{OE}$ to Z or $\overline{Z}$	3.3	1.5	7.0	11.0	1.5	12.0	ns
		5.0	1.5	5.5	8.0	1.5	8.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V.
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

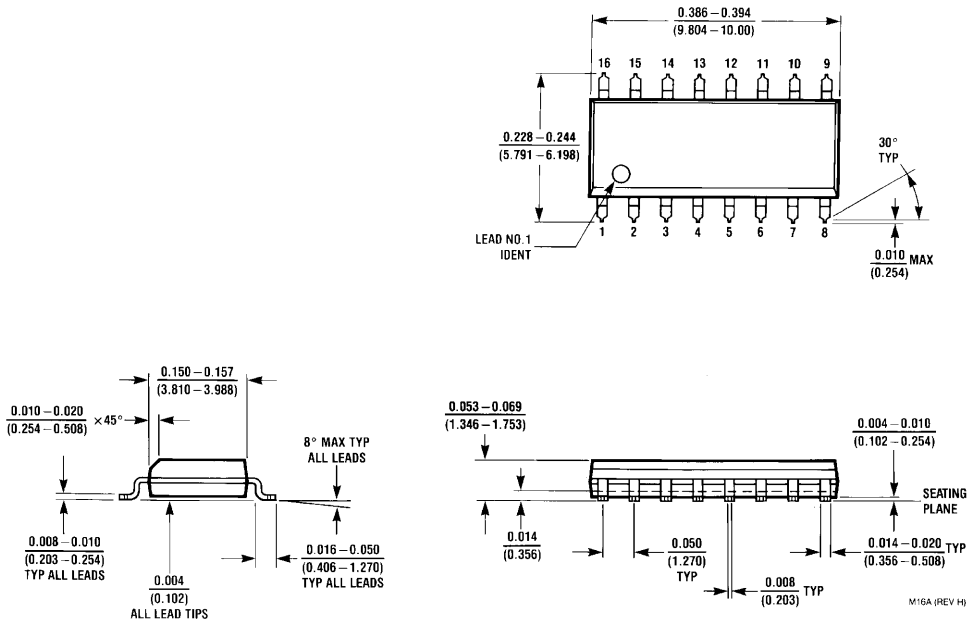
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z or $\overline{Z}$	5.0	2.5	7.0	15.5	2.0	17.0	ns
t_{PHL}	Propagation Delay S_n to Z or $\overline{Z}$	5.0	2.5	7.5	16.5	2.5	18.5	ns
t_{PLH}	Propagation Delay I_n to Z or $\overline{Z}$	5.0	2.5	5.5	12.0	2.0	13.0	ns
t_{PHL}	Propagation Delay I_n to Z or $\overline{Z}$	5.0	2.5	6.5	12.5	2.5	14.0	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to Z or $\overline{Z}$	5.0	1.5	5.0	8.5	1.5	9.0	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to Z or $\overline{Z}$	5.0	1.5	4.5	8.5	1.5	9.5	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to Z or $\overline{Z}$	5.0	2.0	6.0	12.0	2.0	13.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to Z or $\overline{Z}$	5.0	1.5	4.5	8.5	1.5	9.0	ns

Note 8: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

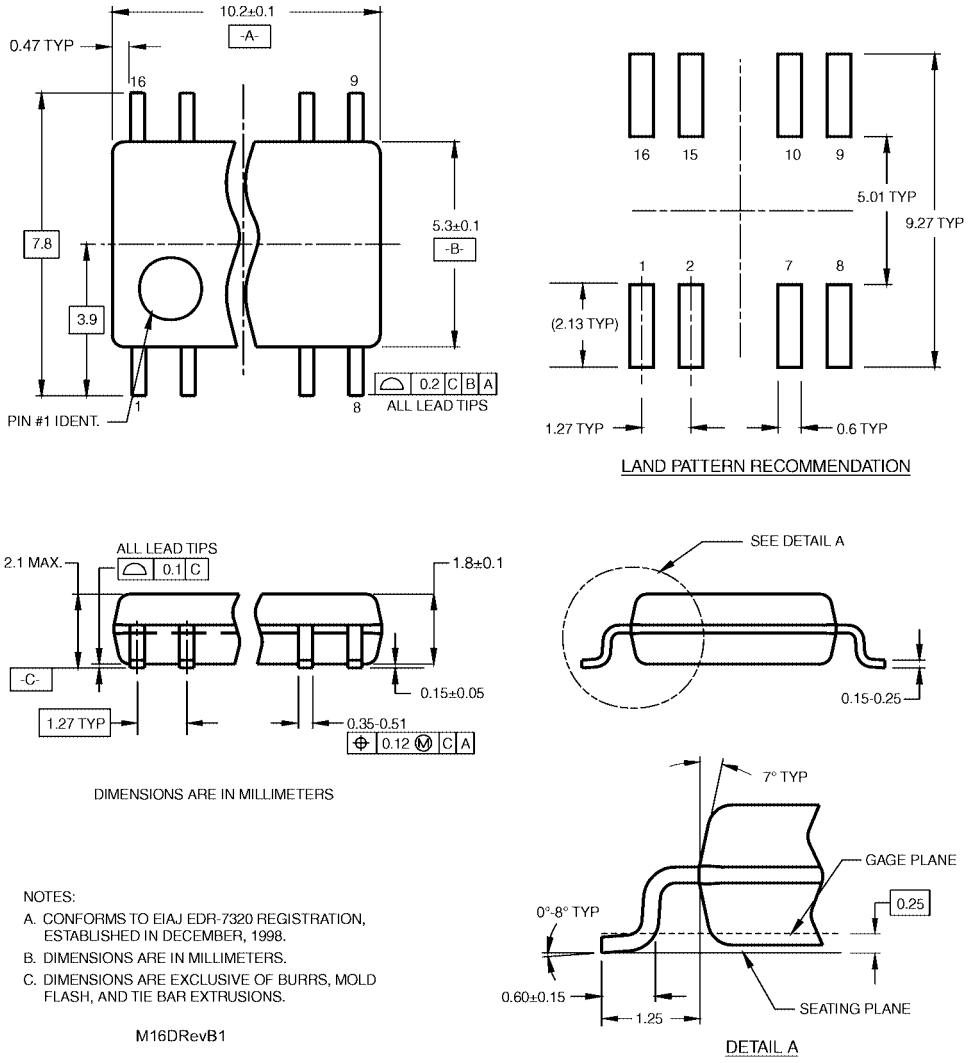
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

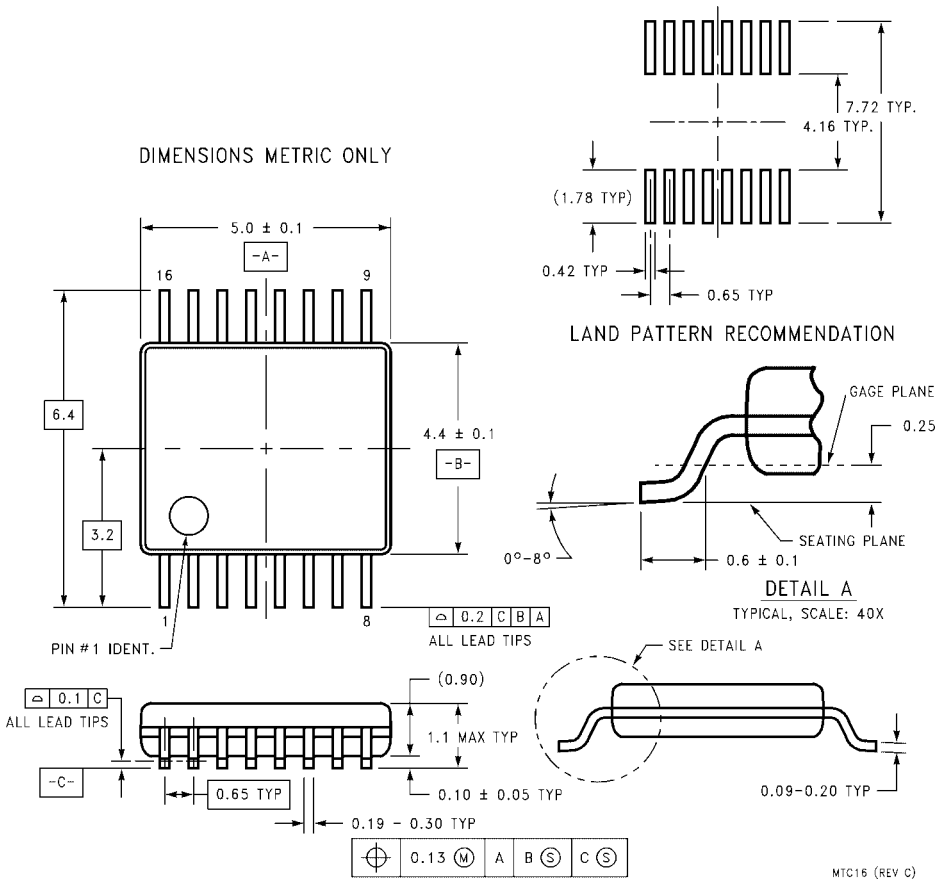
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

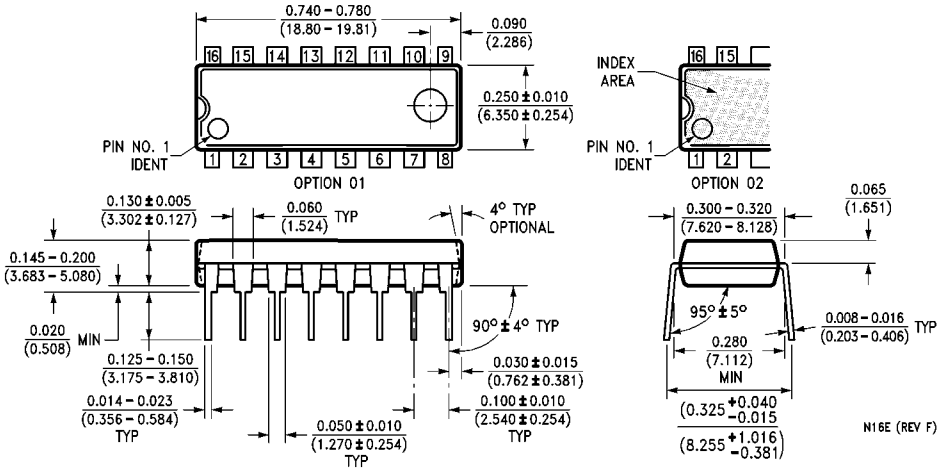
16-Lead Small Outline Package (SOP), EIAJ Type II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Packge (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC253 • 74ACT253
Dual 4-Input Multiplexer with 3-STATE Outputs

General Description

The AC/ACT253 is a dual 4-input multiplexer with 3-STATE outputs. It can select two bits of data from four sources using common select inputs. The outputs may be individually switched to a high impedance state with a HIGH on the respective Output Enable ($\overline{OE}$) inputs, allowing the outputs to interface directly with bus oriented systems.

Features

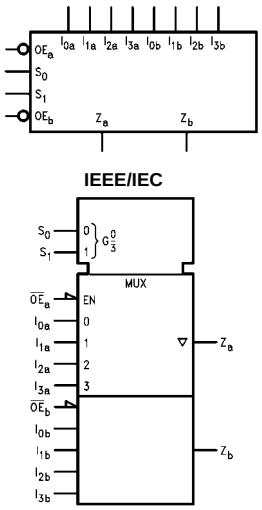
- I_{CC} and I_{OZ} reduced by 50%
- Multifunction capability
- Noninverting 3-STATE outputs
- Outputs source/sink 24 mA
- ACT253 has TTL-compatible inputs

Ordering Code:

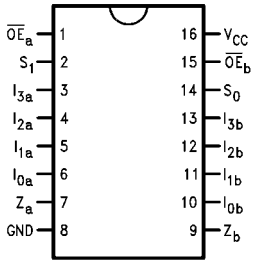
Order Number	Package Number	Package Description
74AC253SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC253SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC253PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT253SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT253SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT253PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Diagrams



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{3a}	Side A Data Inputs
I_{0b}–I_{3b}	Side B Data Inputs
S_0, S_1	Common Select Inputs
$\overline{OE}_a$	Side A Output Enable Input
$\overline{OE}_b$	Side B Output Enable Input
Z_a, Z_b	3-STATE Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The AC/ACT253 contains two identical 4-input multiplexers with 3-STATE outputs. They select two bits from four sources selected by common Select inputs (S_0, S_1). The 4-input multiplexers have individual Output Enable ($\overline{OE}_a$, $\overline{OE}_b$) inputs which, when HIGH, force the outputs to a high impedance (High Z) state. This device is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two select inputs. The logic equations for the outputs are shown:

$$Z_a = \overline{OE}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0)$$

$$Z_b = \overline{OE}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet \overline{S}_0 + I_{3b} \bullet S_1 \bullet S_0)$$

If the outputs of 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-STATE devices whose outputs are tied together are designed so that there is no overlap.

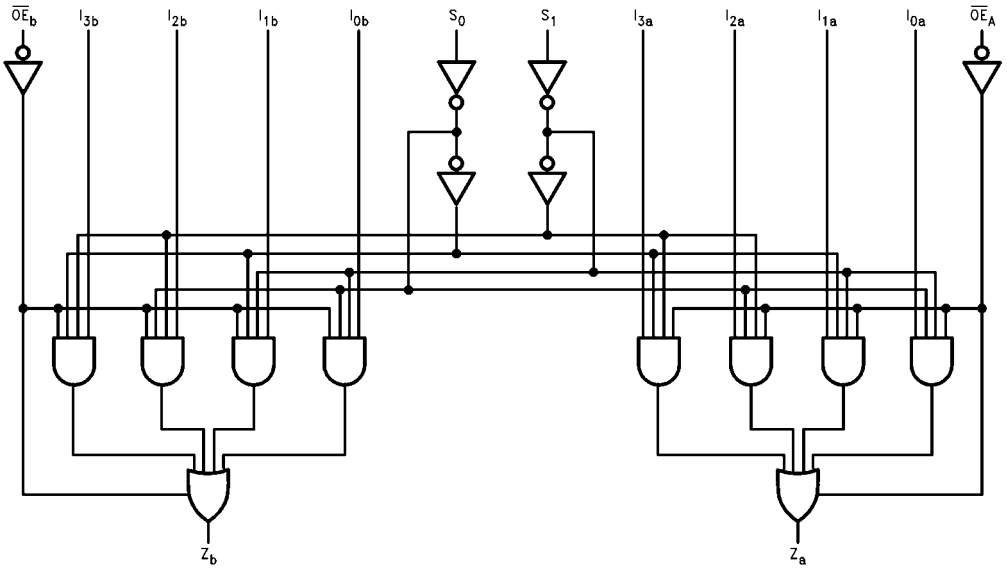
Truth Table

Select Inputs		Data Inputs				Output Enable	Outputs
S_0	S_1	I_0	I_1	I_2	I_3	$\overline{OE}$	Z
X	X	X	X	X	X	H	Z
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
H	L	X	L	X	X	L	L
H	L	X	H	X	X	L	H
L	H	X	X	L	X	L	L
L	H	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Address Inputs S_0 and S_1 are common to both sections.

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	µA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z_n	3.3	2.0	8.5	15.5	2.0	17.5	ns
		5.0	2.0	6.5	11.0	1.5	12.5	
t_{PHL}	Propagation Delay S_n to Z_n	3.3	2.5	9.5	16.0	2.0	18.0	ns
		5.0	2.0	7.0	11.5	1.5	13.0	
t_{PLH}	Propagation Delay I_n to Z_n	3.3	1.5	7.0	14.5	1.5	17.0	ns
		5.0	1.5	5.5	10.0	1.5	11.5	
t_{PHL}	Propagation Delay I_n to Z_n	3.3	2.0	7.5	13.0	1.5	15.0	ns
		5.0	1.5	5.5	9.5	1.5	11.0	
t_{PZH}	Output Enable Time	3.3	1.5	4.5	8.0	1.0	8.5	ns
		5.0	1.5	3.5	6.0	1.0	6.5	
t_{PZL}	Output Enable Time	3.3	1.5	5.0	8.0	1.0	9.0	ns
		5.0	1.5	3.5	6.0	1.0	7.0	
t_{PHZ}	Output Disable Time	3.3	2.0	5.5	9.5	1.5	10.0	ns
		5.0	2.0	5.0	8.0	1.5	8.5	
t_{PLZ}	Output Disable Time	3.3	1.5	5.0	8.0	1.0	9.0	ns
		5.0	1.5	4.0	7.0	1.0	7.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

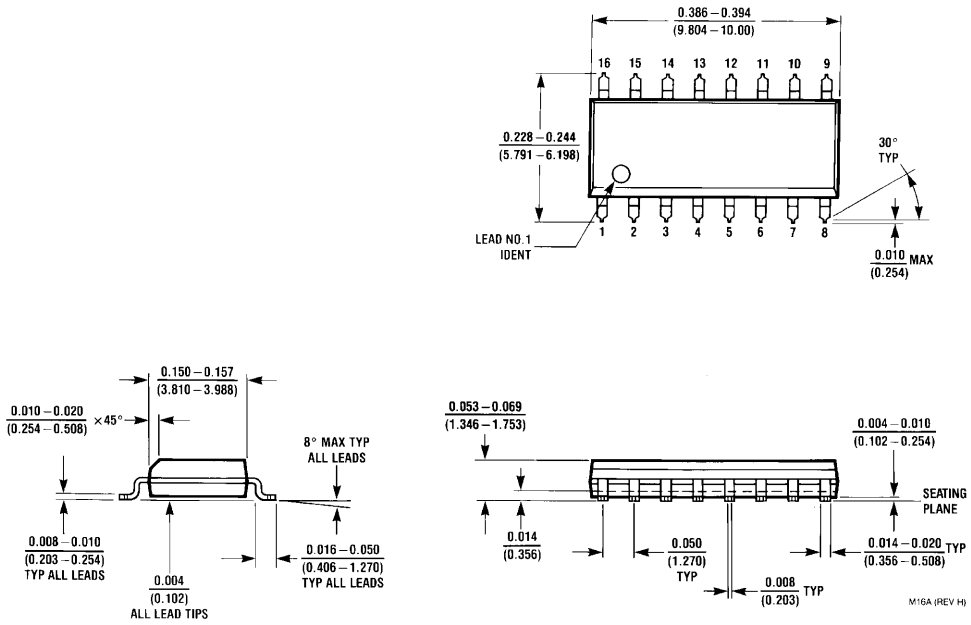
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z_n	5.0	2.0	7.0	11.5	2.0	13.0	ns
t_{PHL}	Propagation Delay S_n to Z_n	5.0	3.0	7.5	13.0	2.5	14.5	ns
t_{PLH}	Propagation Delay I_n to Z_n	5.0	2.5	5.5	10.0	2.0	11.0	ns
t_{PHL}	Propagation Delay I_n to Z_n	5.0	3.5	6.5	11.0	3.0	12.5	ns
t_{PZH}	Output Enable Time	5.0	2.0	4.5	7.5	1.5	8.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	5.0	8.0	1.5	9.0	ns
t_{PHZ}	Output Disable Time	5.0	3.0	6.0	9.5	2.5	10.0	ns
t_{PLZ}	Output Disable Time	5.0	2.5	4.5	7.5	2.0	8.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

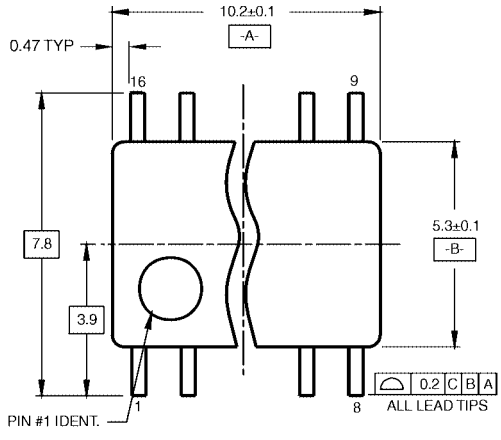
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	50.0	pF	V_{CC} = 5.0V

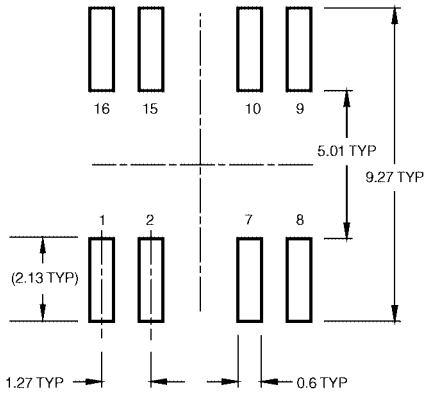
Physical Dimensions inches (millimeters) unless otherwise noted



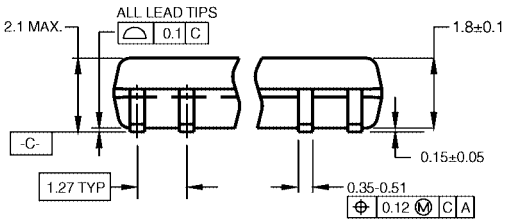
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

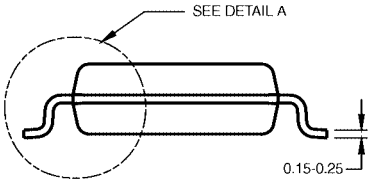
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



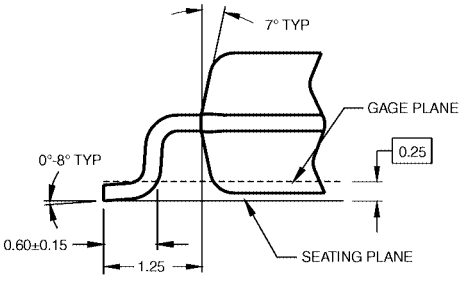


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

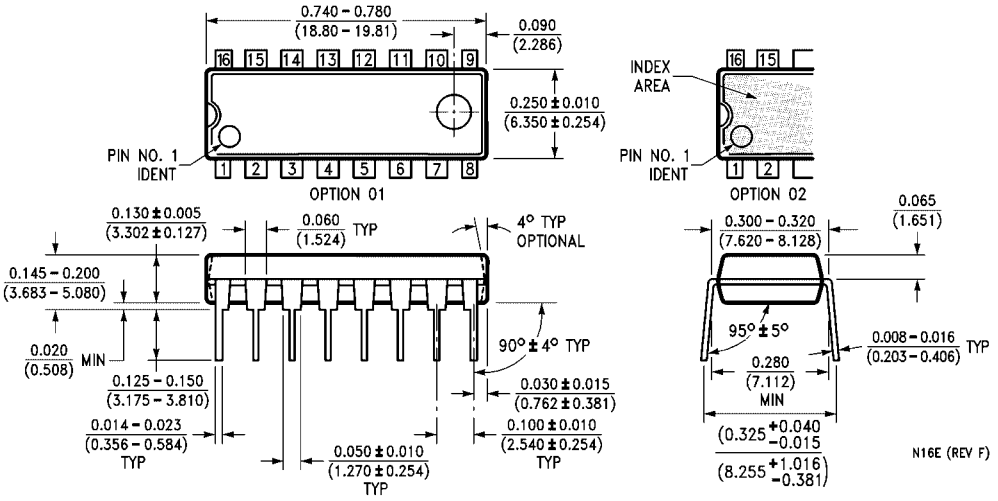
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC257 • 74ACT257
Quad 2-Input Multiplexer with 3-STATE Outputs

General Description

The AC/ACT257 is a quad 2-input multiplexer with 3-STATE outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (noninverted) form. The outputs may be switched to a high impedance state by placing a logic HIGH on the common Output Enable ($\overline{OE}$) input, allowing the outputs to interface directly with bus-oriented systems.

Features

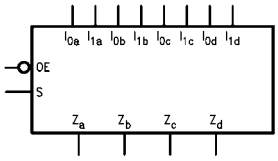
- I_{CC} and I_{OZ} reduced by 50%
- Multiplexer expansion by tying outputs together
- Noninverting 3-STATE outputs
- Outputs source/sink 24 mA
- ACT257 has TTL-compatible inputs

Ordering Code:

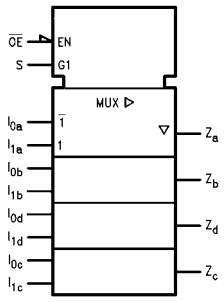
Order Number	Package Number	Package Description
74AC257SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74AC257SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC257MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC257PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT257SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT257SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT257MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT257PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

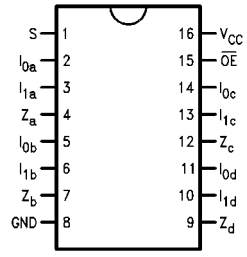
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
S	Common Data Select Input
$\overline{OE}$	3-STATE Output Enable Input
I_{0a}–I_{0d}	Data Inputs from Source 0
I_{1a}–I_{1d}	Data Inputs from Source 1
Z_a–Z_d	3-STATE Multiplexer Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The AC/ACT257 is quad 2-input multiplexer with 3-STATE outputs. It selects four bits of data from two sources under control of a Common Data Select input. When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The data on the selected inputs appears at the outputs in true (noninverted) form. The device is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are as follows:

$$Z_a = \overline{OE} \bullet (1_{1a} \bullet S + I_{0a} \bullet \overline{S})$$

$$Z_b = \overline{OE} \bullet (1_{1b} \bullet S + I_{0b} \bullet \overline{S})$$

$$Z_c = \overline{OE} \bullet (1_{1c} \bullet S + I_{0c} \bullet \overline{S})$$

$$Z_d = \overline{OE} \bullet (1_{1d} \bullet S + I_{0d} \bullet \overline{S})$$

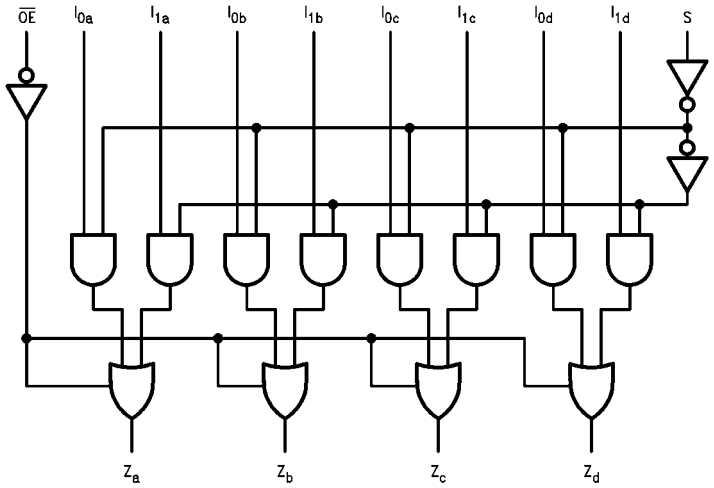
When the Output Enable ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure the Output Enable signals to 3-STATE devices whose outputs are tied together are designed so there is no overlap.

Truth Table

Output Enable	Select Input	Data Inputs		Outputs
$\overline{OE}$	S	I_0	I_1	Z
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source ort	
Sink Curren (I_O)	±50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Voltage Input	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Voltage Input	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Voltage Output	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Voltage Output	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Dynamic Output Current	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Minimum (Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay I_n to Z_n	3.3	1.5	5.0	8.5	1.0	9.0	ns
		5.0	1.5	4.0	6.0	1.0	7.0	
t_{PHL}	Propagation Delay I_n to Z_n	3.3	1.5	6.0	8.5	1.0	9.0	ns
		5.0	1.5	4.5	6.0	1.0	7.0	
t_{PLH}	Propagation Delay S to Z_n	3.3	1.5	7.0	10.5	1.5	11.5	ns
		5.0	1.5	5.0	7.5	1.0	8.5	
t_{PHL}	Propagation Delay S to Z_n	3.3	1.5	7.5	10.5	1.5	11.5	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t_{PZH}	Output Enable Time	3.3	1.5	6.5	9.5	1.0	10.5	ns
		5.0	1.5	5.0	7.5	1.0	8.5	
t_{PZL}	Output Enable Time	3.3	1.5	5.5	9.0	1.0	10.0	ns
		5.0	1.5	5.0	8.5	1.0	9.5	
t_{PHZ}	Output Disable Time	3.3	1.5	5.5	10.0	1.0	11.0	ns
		5.0	1.5	5.0	9.0	1.0	10.0	
t_{PLZ}	Output Disable Time	3.3	1.5	5.5	9.0	1.0	10.0	ns
		5.0	1.5	5.0	8.0	1.0	9.0	

Note 7: Voltage Range 3.3 is 3.0V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

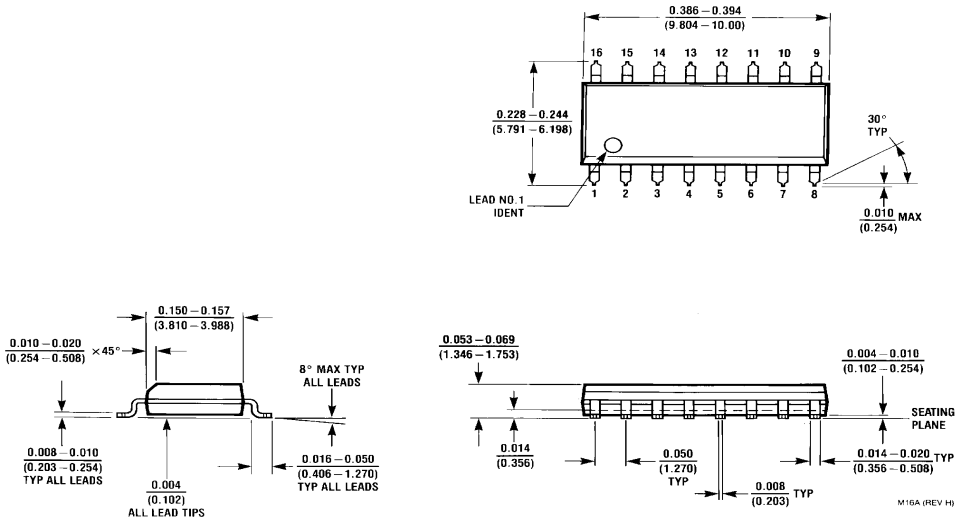
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay I_n to Z_n	5.0	1.5	5.0	7.0	1.0	7.5	ns
t_{PHL}	Propagation Delay I_n to Z_n	5.0	2.0	6.0	7.5	1.5	8.5	ns
t_{PLH}	Propagation Delay S to Z_n	5.0	2.0	7.0	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay S to Z_n	5.0	2.5	7.0	10.5	2.0	11.5	ns
t_{PZH}	Output Enable Time	5.0	2.0	6.0	8.0	1.5	9.0	ns
t_{PZL}	Output Enable Time	5.0	2.0	6.0	8.0	1.5	9.0	ns
t_{PHZ}	Output Disable Time	5.0	2.5	6.5	9.0	1.5	10.0	ns
t_{PLZ}	Output Disable Time	5.0	2.0	6.0	7.5	1.5	8.5	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

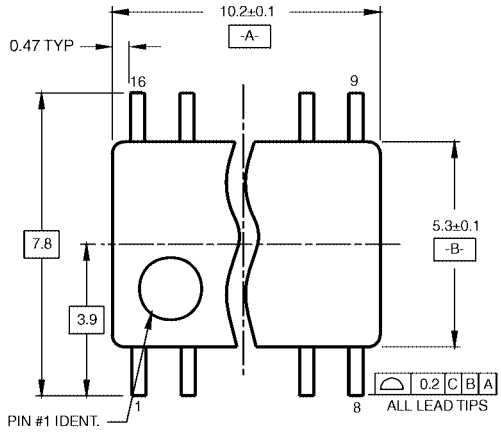
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	50.0	pF	V_{CC} = 5.0V

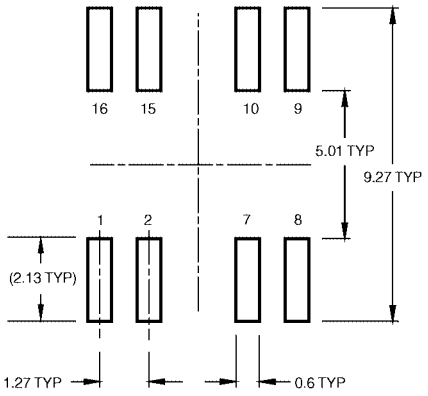
Physical Dimensions inches (millimeters) unless otherwise noted



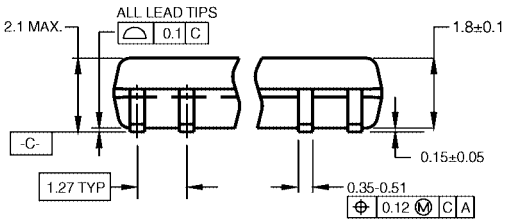
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

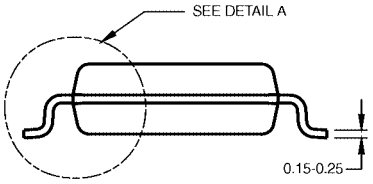
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



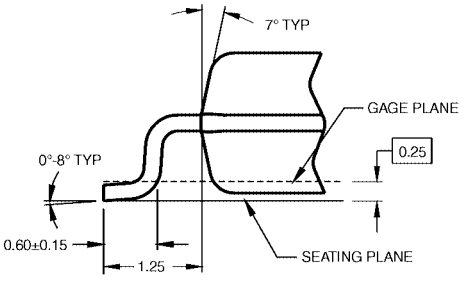


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

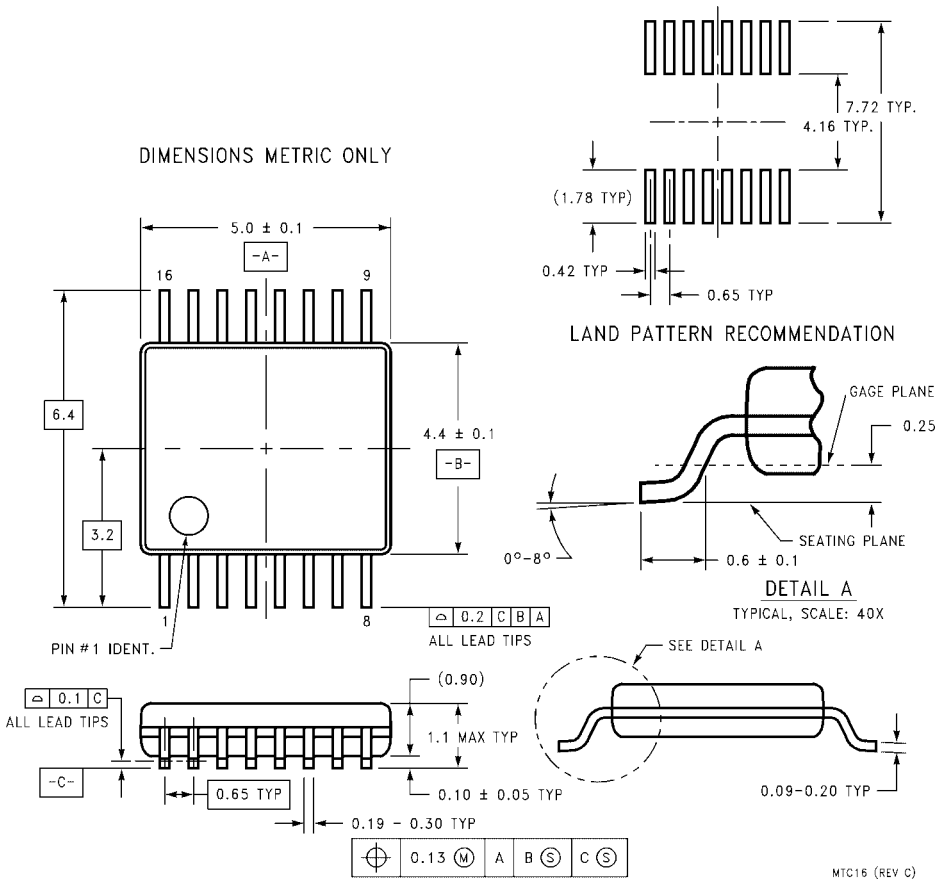
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

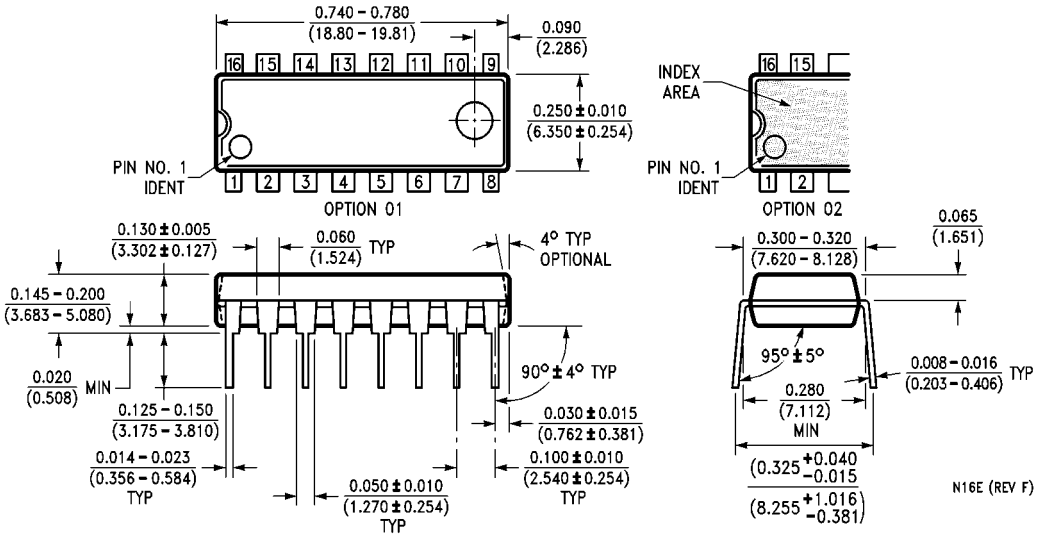
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised October 1999

74AC273 • 74ACT273
Octal D-Type Flip-Flop

General Description

The AC273 and ACT273 have eight edge-triggered D-type flip-flops with individual D-type inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) input load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D-type input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

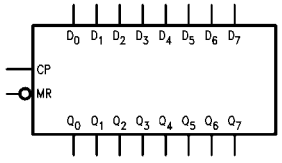
- Ideal buffer for microprocessor or memory
- Eight edge-triggered D-type flip-flops
- Buffered common clock
- Buffered, asynchronous master reset
- See 377 for clock enable version
- See 373 for transparent latch version
- See 374 for 3-STATE version
- Outputs source/sink 24 mA
- 74ACT273 has TTL-compatible inputs

Ordering Code:

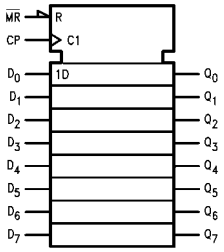
Order Number	Package Number	Package Description
74AC273SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC273PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT273SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT273PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

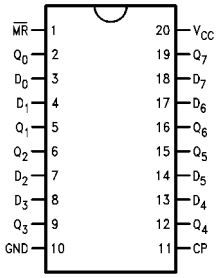
Logic Symbols



IEEE/IEC



Connection Diagram



FACT™ is a trademark of Fairchild Semiconductor Corporation.

Pin Descriptions

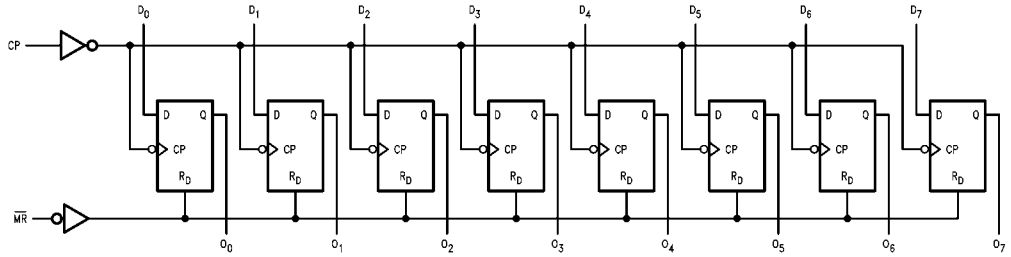
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

Mode Select-Function Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load '1'	H	⌐	H	H
Load '0'	H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J) (PDIP)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V for AC	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V for ACT	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	3.3	90	125		75		MHz
		5.0	140	175		125		
t_{PLH}	Propagation Delay Clock to Output	3.3	4.0	7.0	12.5	3.0	14.0	ns
		5.0	3.0	5.5	9.0	2.5	10.0	
t_{PHL}	Propagation Delay Clock to Output	3.3	4.0	7.0	13.0	3.5	14.5	ns
		5.0	3.0	5.0	10.0	2.5	11.0	
t_{PHL}	Propagation Delay $\overline{MR}$ to Output	3.3	4.0	7.0	13.0	3.5	14.0	ns
		5.0	3.0	5.0	10.0	2.5	10.5	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW Data to CP	3.3	3.5	5.5	6.0	ns
		5.0	2.5	4.0	4.5	
t_H	Hold Time, HIGH or LOW Data to CP	3.3	−2.0	0	0	ns
		5.0	−1.0	1.0	1.0	
t_W	Clock Pulse Width HIGH or LOW	3.3	3.5	5.5	6.0	ns
		5.0	2.5	4.0	4.5	
t_W	$\overline{MR}$ Pulse Width HIGH or LOW	3.3	2.0	5.5	6.0	ns
		5.0	1.5	4.0	4.5	
t_{rec}	Recovery Time $\overline{MR}$ to CP	3.3	1.5	3.5	4.5	ns
		5.0	1.0	2.0	3.0	

Note 6: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 7)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 7)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 8)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 7: All outputs loaded; thresholds on input associated with output under test.

Note 8: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	2.0	125	189		110		MHz
t_{PLH} t_{PHL}	Propagation Delay CP to Q_n	5.0	1.5	6.5	8.5	1.5	9.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	1.5	7.0	9.0	1.5	8.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

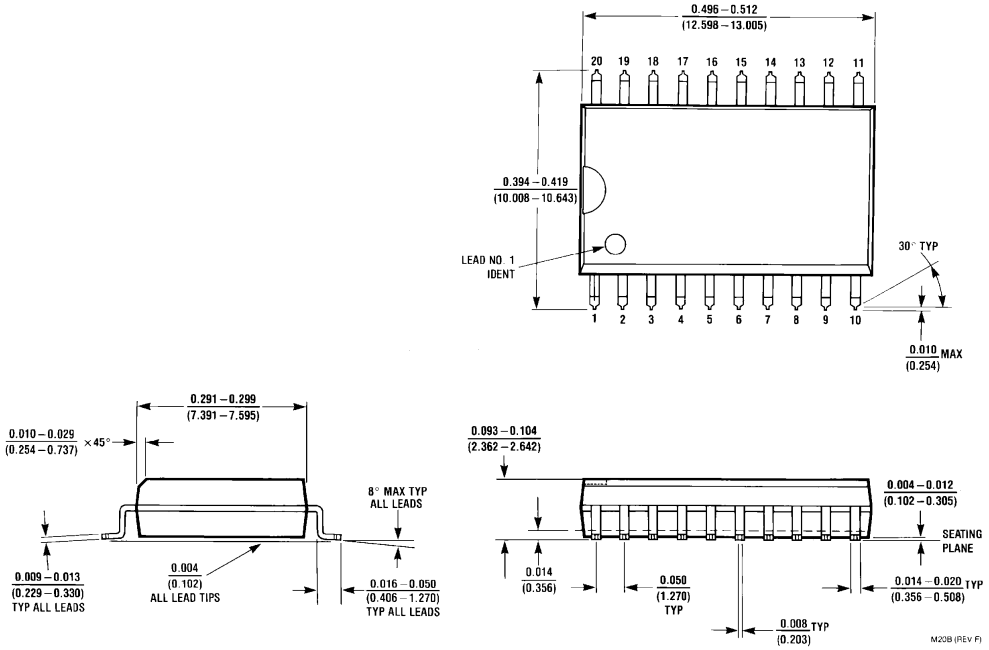
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	1.0	3.5	3.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	−0.5	1.5	1.5	ns
t_W	Clock Pulse Width HIGH or LOW	5.0	2.0	4.0	4.0	ns
t_W	$\overline{MR}$ Pulse Width HIGH or LOW	5.0	1.5	4.0	4.0	ns
t_W	Recovery Time $\overline{MR}$ to CP	5.0	0.5	3.0	3.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

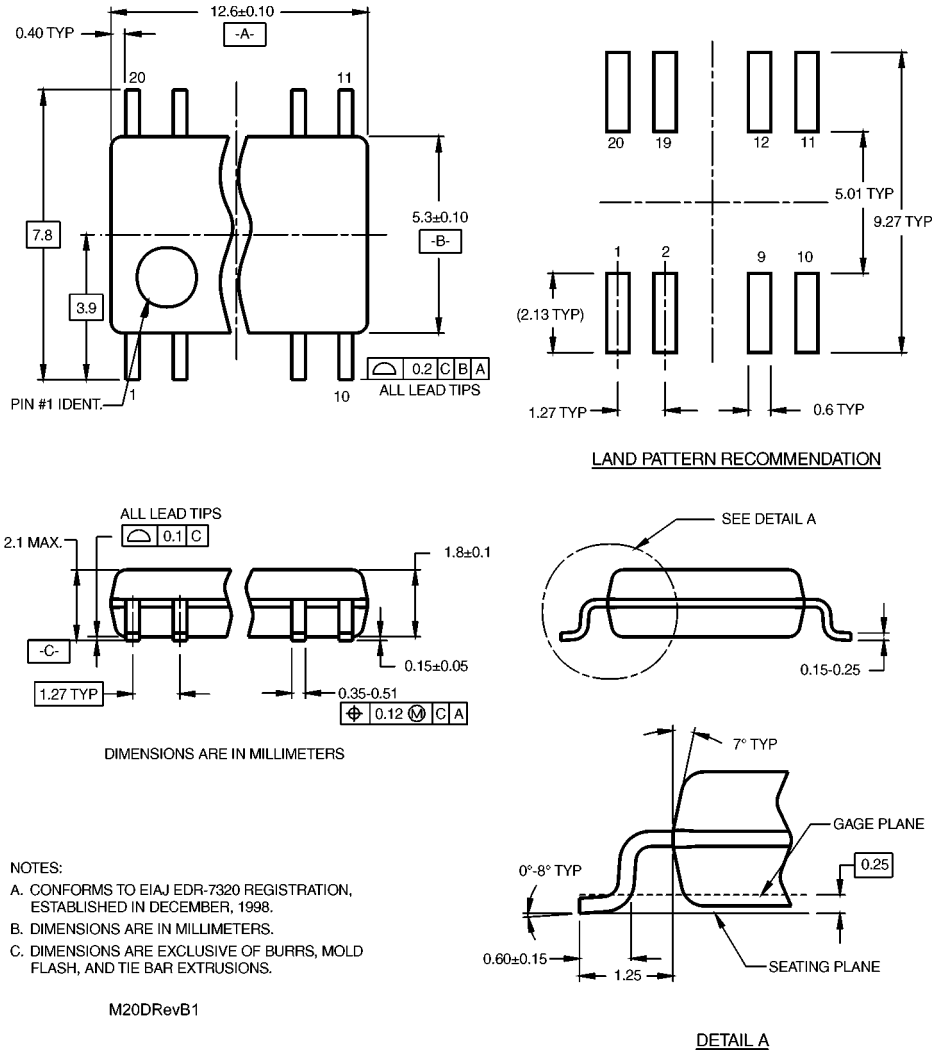
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance for AC	50.0	pF	V_{CC} = 5.0V
	Power Dissipation Capacitance for ACT	40.0		

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

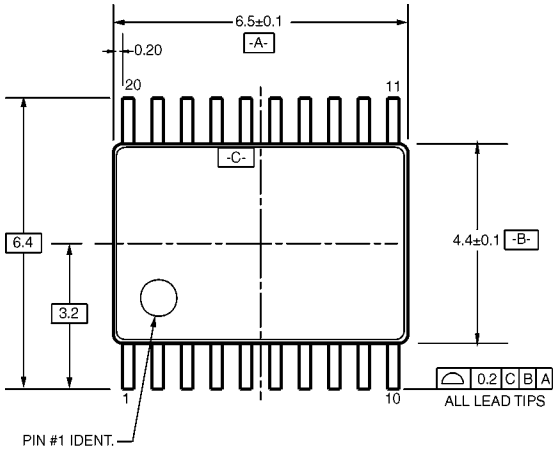
B. DIMENSIONS ARE IN MILLIMETERS.

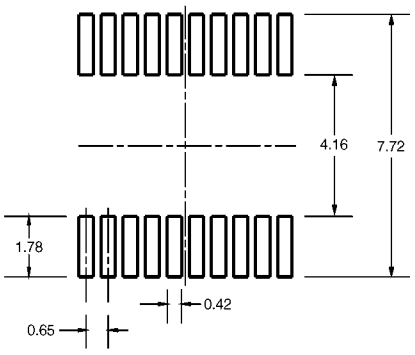
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

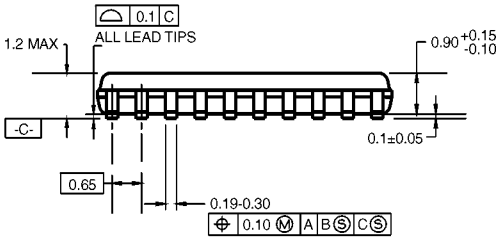
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

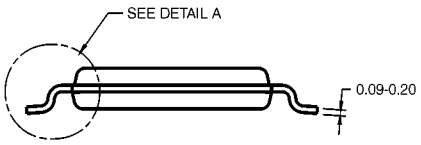
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

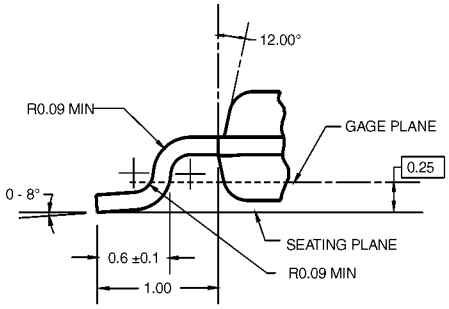
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

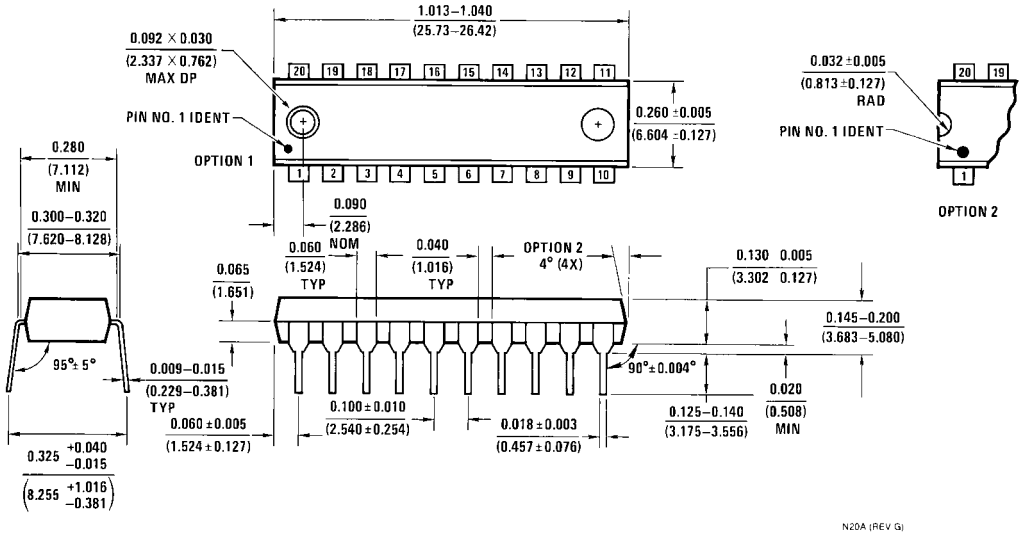
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC280
9-Bit Parity Generator/Checker

General Description

The AC280 is a high-speed parity generator/checker that accepts nine bits of input data and detects whether an even or an odd number of these inputs is HIGH. If an even number of inputs is HIGH, the Sum Even output is HIGH. If an odd number is HIGH, the Sum Even output is LOW. The Sum Odd output is the complement of the Sum Even output.

Features

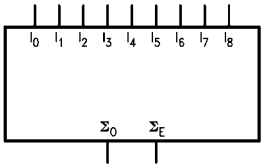
- I_{CC} reduced by 50%
- 9-bit width for memory applications
- AC280: 5962-92201

Ordering Code:

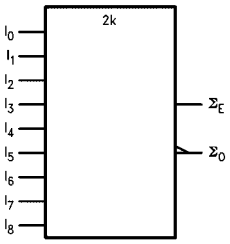
Order Number	Package Number	Package Description
74AC280SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC280SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

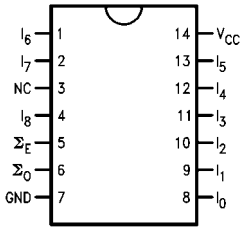
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_0–I_8	Data Inputs
Σ_O	Odd Parity Output
Σ_E	Even Parity Output

Truth Table

Number of HIGH Inputs I_0–I_8	Outputs	
	Σ Even	Σ Odd
0, 2, 4, 6, 8	H	L
1, 3, 5, 7, 9	L	H

H = HIGH Voltage Level
L = LOW Voltage Level

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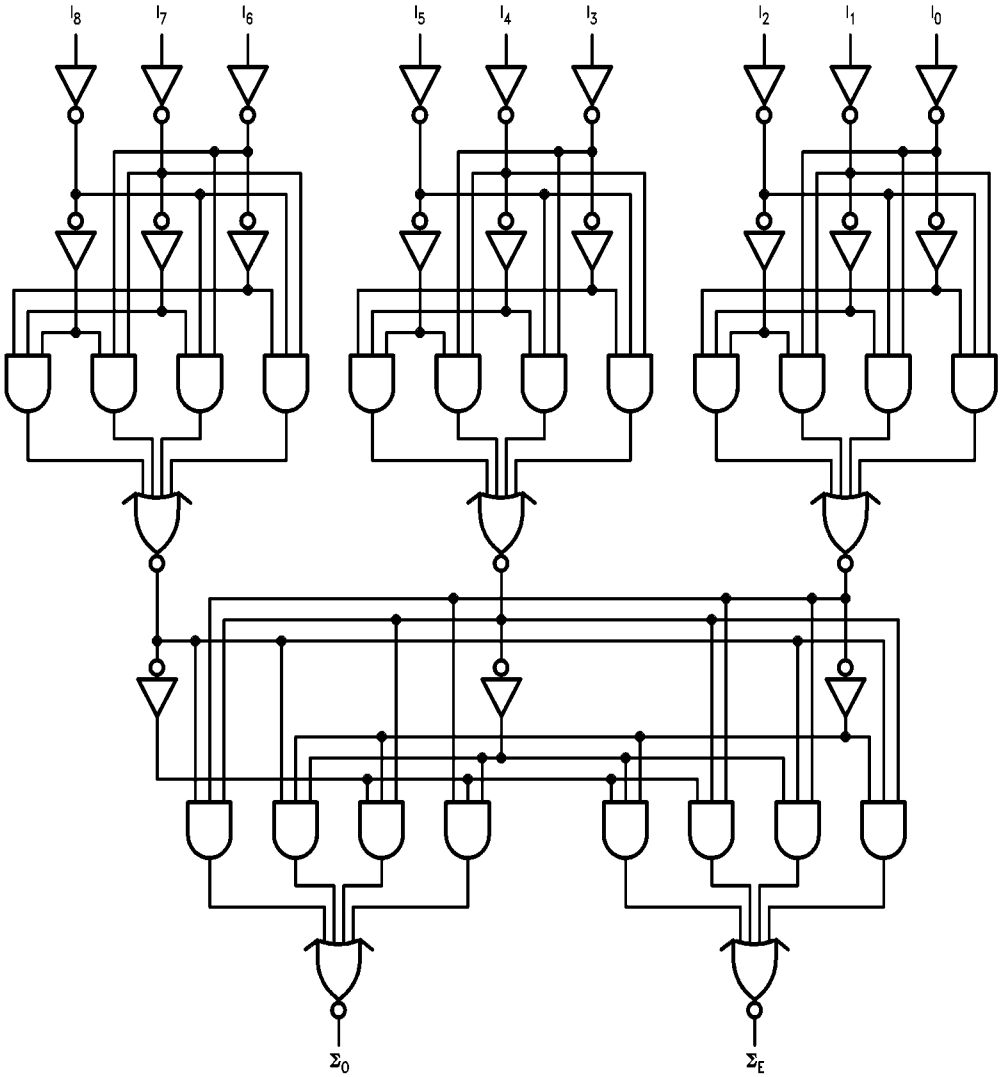
Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, output/input loading variables. Fairchild does not recommend operation of FACT circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = +25°C Guaranteed Limits	T_A = −40°C to +85°C Guaranteed Limits	Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	5.0	10.5	17.0	4.0	18.5	ns
t_{PHL}	I_n to Σ_E	5.0	3.0	7.5	13.0	2.0	14.5	
t_{PLH}	Propagation Delay	3.3	5.0	12.0	17.0	4.0	18.5	ns
t_{PHL}	I_n to Σ_O	5.0	3.0	8.5	13.0	2.0	14.5	

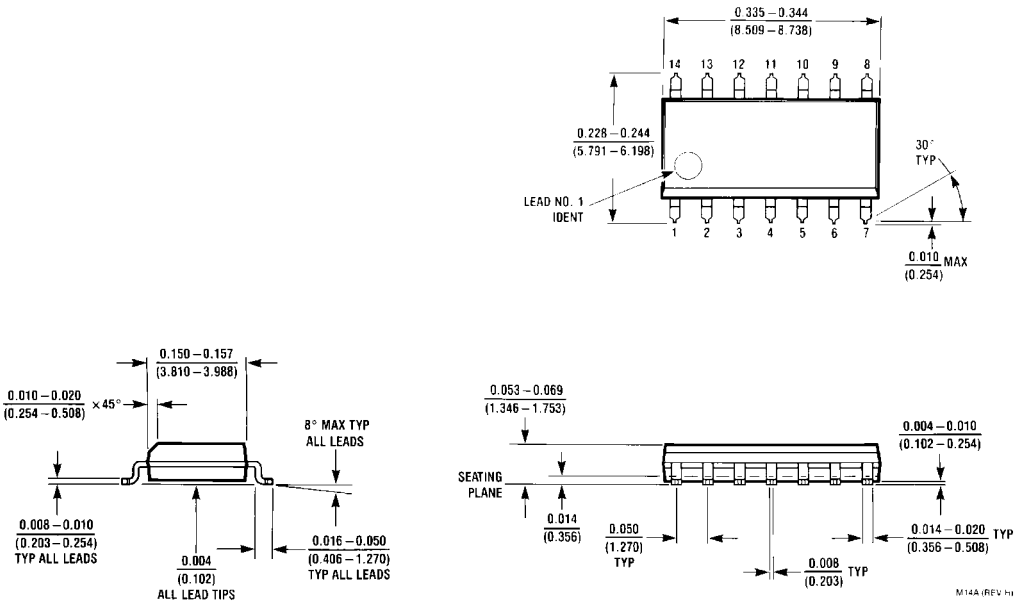
Note 5: Voltage range 3.3 is 3.3V ± 0.3V.

Voltage range 5.0 is 5.0V ± 0.5V.

Capacitance

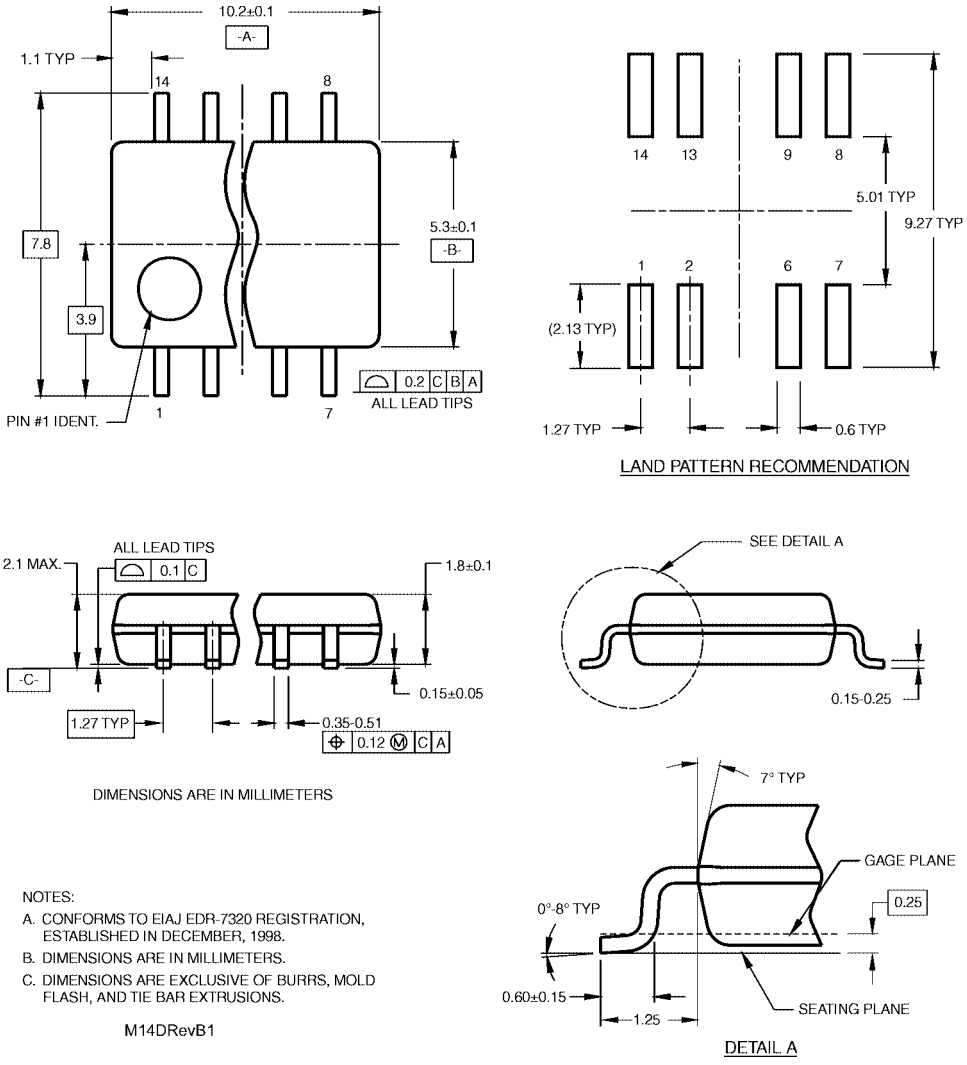
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	75.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

July 1988
Revised November 1999

74AC299 • 74ACT299
8-Input Universal Shift/Storage Register with Common Parallel I/O Pins

General Description

The AC/ACT299 is an 8-bit universal shift/storage register with 3-STATE outputs. Four modes of operation are possible: hold (store), shift left, shift right and load data. The parallel load inputs and flip-flop outputs are multiplexed to reduce the total number of package pins. Additional outputs are provided for flip-flops Q_0, Q_7 to allow easy serial cascading. A separate active LOW Master Reset is used to reset the register.

Features

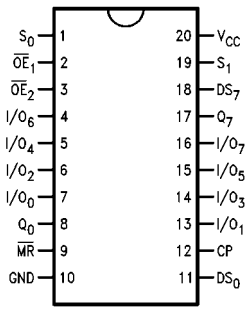
- I_{CC} and I_{OZ} reduced by 50%
- Common parallel I/O for reduced pin count
- Additional serial inputs and outputs for expansion
- Four operating modes: shift left, shift right, load and store
- 3-STATE outputs for bus-oriented applications
- Outputs source/sink 24 mA
- ACT299 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC299SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC299SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC299MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC299PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT299SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT299MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT299PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
CP	Clock Pulse Input
DS_0	Serial Data Input for Right Shift
DS_7	Serial Data Input for Left Shift
S_0, S_1	Mode Select Inputs
$\overline{MR}$	Asynchronous Master Reset
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I/O_0–I/O_7	Parallel Data Inputs or 3-STATE Parallel Outputs
Q_0, Q_7	Serial Outputs

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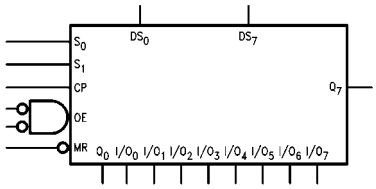
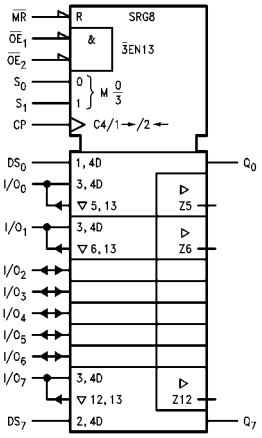
Logic Symbols



IEEE/IEC



Truth Table

Inputs				Response
$\overline{MR}$	S_1	S_0	CP	
L	X	X	X	Asynchronous Reset; Q_0–Q_7 = LOW
H	H	H	⌐	Parallel Load; $I/O_n \rightarrow Q_n$
H	L	H	⌐	Shift Right; $DS_0 \rightarrow Q_0$, $Q_0 \rightarrow Q_1$, etc.
H	H	L	⌐	Shift Left, $DS_7 \rightarrow Q_7$, $Q_7 \rightarrow Q_6$, etc.
H	L	L	X	Hold

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

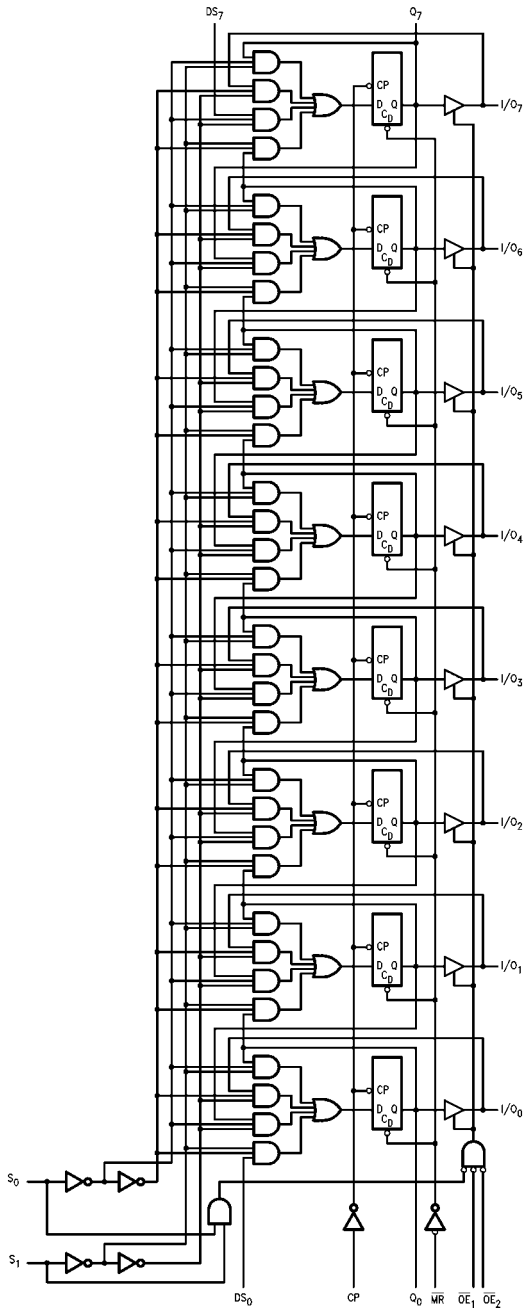
Functional Description

The AC/ACT299 contains eight edge-triggered D-type flip-flops and the interstage logic necessary to perform synchronous shift left, shift right, parallel load and hold operations. The type of operation is determined by S_0 and S_1, as shown in the Truth Table. All flip-flop outputs are brought out through 3-STATE buffers to separate I/O pins that also serve as data inputs in the parallel load mode. Q_0 and Q_7 are also brought out on other pins for expansion in serial shifting of longer words.

A LOW signal on $\overline{MR}$ overrides the Select and CP inputs and resets the flip-flops. All other state changes are initiated by the rising edge of the clock. Inputs can change when the clock is in either state provided only that the recommended setup and hold times, relative to the rising edge of CP, are observed.

A HIGH signal on either $\overline{OE}_1$ or $\overline{OE}_2$ disables the 3-STATE buffers and puts the I/O pins in the high impedance state. In this condition the shift, hold, load and reset operations can still occur. The 3-STATE buffers are also disabled by HIGH signals on both S_0 and S_1 in preparation for a parallel load operation.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
(PDIP)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
(Unless Otherwise Specified)	
AC	2.0V to 6.0V
ACT	4.5V to 5.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. Obviously the databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}	T_A = 25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OH} = 12 mA
		4.5		0.36	0.44	V	I_{OH} = 24 mA
		5.5		0.36	0.44		I_{OH} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			86	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

DC Electrical Characteristics for AC (Continued)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
I_{OZT}	Maximum I/O Leakage Current	5.5		± 0.3	± 3.0	µA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

Note 2: All outputs loaded; threshold on input associated with output under test.

Note 3: Maximum test duration 20 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level Input Voltage	3.0 4.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 µA
		4.5 5.5	0.0001	3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 µA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL}= 24 mA I_{OL}= 24 mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 6)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.3	±3.0	µA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Input	3.3	90	124		80		MHz
	Frequency	5.0	130	173		105		
t_{PLH}	Propagation Delay	3.3	8.5	14.0	20.5	7.0	22.0	ns
	CP to Q_0 or Q_7 (Shift Left or Right)	5.0	5.5	9.5	14.0	4.5	15.0	
t_{PHL}	Propagation Delay	3.3	8.5	14.5	21.5	7.0	23.0	ns
	CP to Q_0 or Q_7 (Shift Left or Right)	5.0	5.5	10.0	14.5	5.0	16.0	
t_{PLH}	Propagation Delay	3.3	9.0	14.5	20.5	7.5	22.5	ns
	$\overline{CP}$ to I/O_n	5.0	6.0	10.0	14.5	5.0	16.0	
t_{PHL}	Propagation Delay	3.3	10.0	16.0	23.0	8.5	24.5	ns
	$\overline{CP}$ to I/O_n	5.0	6.5	11.0	16.0	6.0	17.5	
t_{PHL}	Propagation Delay	3.3	9.0	15.5	22.5	7.5	25.0	ns
	$\overline{MR}$ to Q_0 or Q_7	5.0	5.5	10.5	15.5	5.0	17.0	
t_{PHL}	Propagation Delay	3.3	9.0	15.0	21.5	7.5	24.0	ns
	$\overline{MR}$ to I/O_n	5.0	5.5	10.0	15.0	5.0	16.5	
t_{PZH}	Output Enable Time	3.3	7.0	12.0	18.0	6.0	19.5	ns
	$\overline{OE}$ to I/O_n	5.0	4.5	8.5	12.5	4.0	13.5	
t_{PZL}	Output Enable Time	3.3	7.0	12.5	18.0	6.0	20.5	ns
	$\overline{OE}$ to I/O_n	5.0	5.0	8.0	12.5	4.0	14.0	
t_{PHZ}	Output Disable Time	3.3	6.5	13.0	18.5	5.5	19.5	ns
	$\overline{OE}$ to I/O_n	5.0	3.5	9.5	14.0	3.0	15.0	
t_{PLZ}	Output Disable Time	3.3	5.5	11.5	17.0	4.5	19.0	ns
	$\overline{OE}$ to I/O_n	5.0	3.5	8.0	12.5	2.0	13.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V.
Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	3.0	8.0	8.5	ns
	S_0 or S_1 to CP	5.0	2.0	5.0	5.5	
t_H	Hold Time, HIGH or LOW	3.3	−3.0	0.5	0.5	ns
	S_0 or S_1 to CP	5.0	−1.5	1.0	1.0	
t_S	Setup Time, HIGH or LOW	3.3	2.0	5.5	6.0	ns
	I/O_n to CP	5.0	1.0	3.5	4.0	
t_H	Hold Time, HIGH or LOW	3.3	−2.0	0	0	ns
	I/O_n to CP	5.0	−1.0	1.0	1.0	
t_S	Setup Time, HIGH or LOW	3.3	2.5	6.5	7.0	ns
	DS_0 or DS_7 to CP	5.0	1.5	4.0	4.5	
t_H	Hold Time, HIGH or LOW	3.3	−2.0	0	0.5	ns
	DS_0 or DS_7 to CP	5.0	−1.0	1.0	1.0	
t_W	CP Pulse Width, LOW	3.3	3.5	4.5	5.0	ns
		5.0	2.0	3.5	3.5	
t_W	$\overline{MR}$ Pulse Width, LOW	3.3	4.0	4.5	5.0	ns
		5.0	2.0	3.5	3.5	
t_{REC}	Recovery Time	3.3	0	1.5	1.5	ns
	$\overline{MR}$ to CP	5.0	0.5	1.5	1.5	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Input Frequency	5.0	120	170		110		MHz
t_{PLH}	Propagation Delay CP to Q_0 or Q_7 (Shift Left or Right)	5.0	4.0	8.5	12.5	3.0	14.0	ns
t_{PHL}	Propagation Delay CP to Q_0 or Q_7 (Shift Left or Right)	5.0	4.0	9.0	13.5	3.5	15.0	ns
t_{PLH}	Propagation Delay CP to I/O_n	5.0	4.5	8.5	12.5	4.5	13.5	ns
t_{PHL}	Propagation Delay CP to I/O_n	5.0	5.0	9.5	15.0	4.5	16.5	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_0 or Q_7	5.0	4.0	14.0	15.0	4.0	18.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to I/O_n	5.0	4.0	13.0	14.5	3.5	17.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to I/O_n	5.0	2.5	8.0	12.0	1.5	13.0	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to I/O_n	5.0	2.0	8.0	12.0	1.5	13.5	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to I/O_n	5.0	2.0	8.5	12.5	2.0	13.5	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to I/O_n	5.0	2.5	8.0	11.5	2.0	12.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

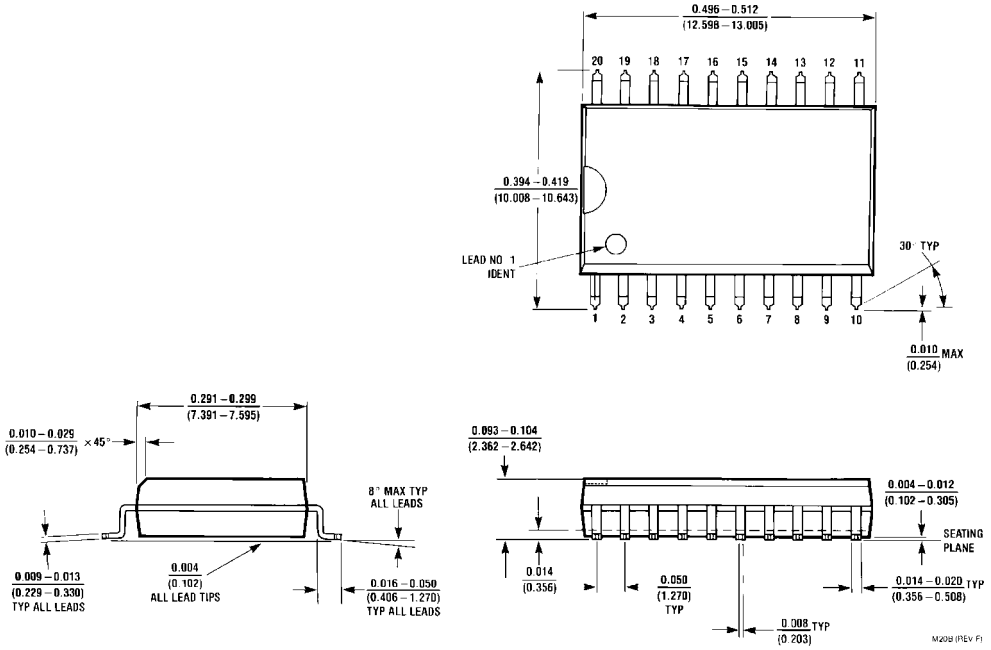
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW S_0 or S_1 to CP	5.0	2.0	5.0	5.5	ns
t_H	Hold Time, HIGH or LOW S_0 or S_1 to CP	5.0	−2.0	1.0	1.0	ns
t_S	Setup Time, HIGH or LOW I/O_n to CP	5.0	1.5	4.0	4.5	ns
t_H	Hold Time, HIGH or LOW I/O_n to CP	5.0	−1.0	1.0	1.0	ns
t_S	Setup Time, HIGH or LOW DS_0 or DS_7 to CP	5.0	1.5	4.5	5.0	ns
t_H	Hold Time, HIGH or LOW DS_0 or DS_7 to CP	5.0	−1.0	1.0	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.0	4.0	4.5	ns
t_W	$\overline{MR}$ Pulse Width, LOW	5.0	2.0	3.5	3.5	ns
t_{REC}	Recovery Time, $\overline{MR}$ to CP	5.0	0	1.5	1.5	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

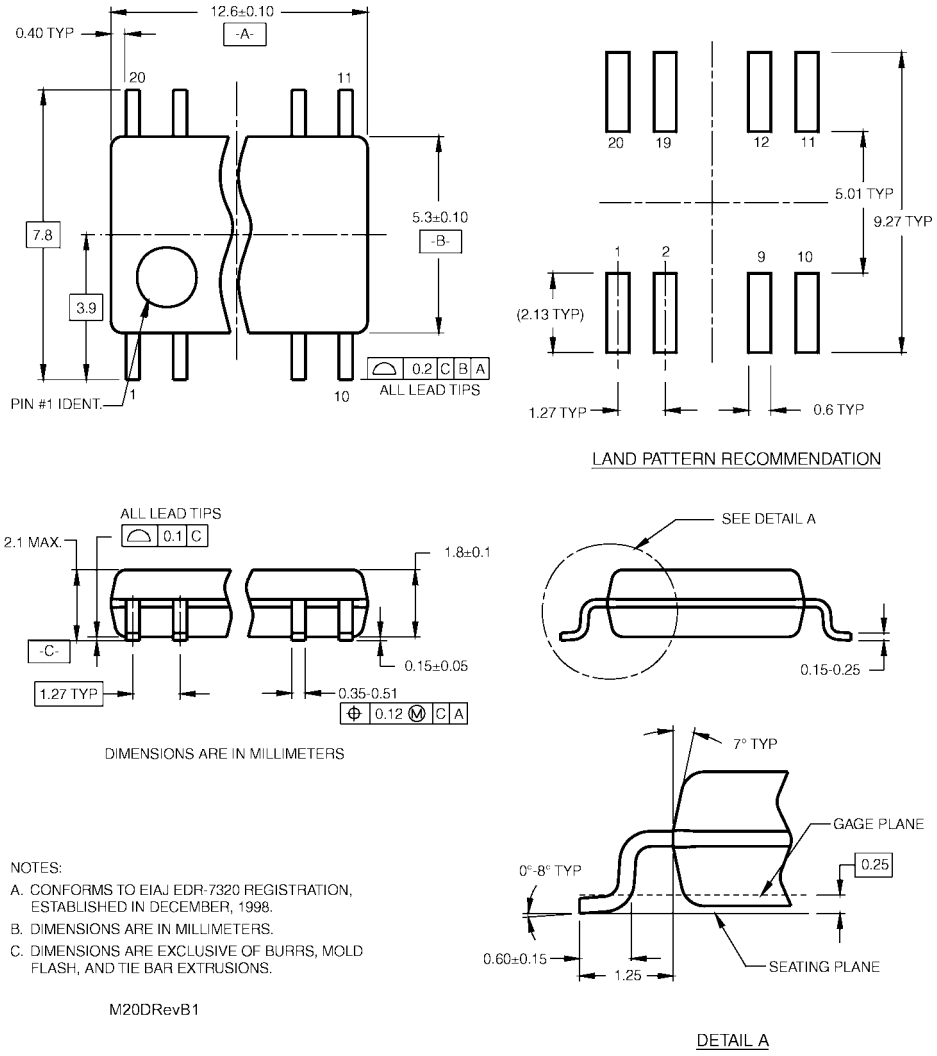
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	170	pF	$V_{CC} = 5.5V$

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

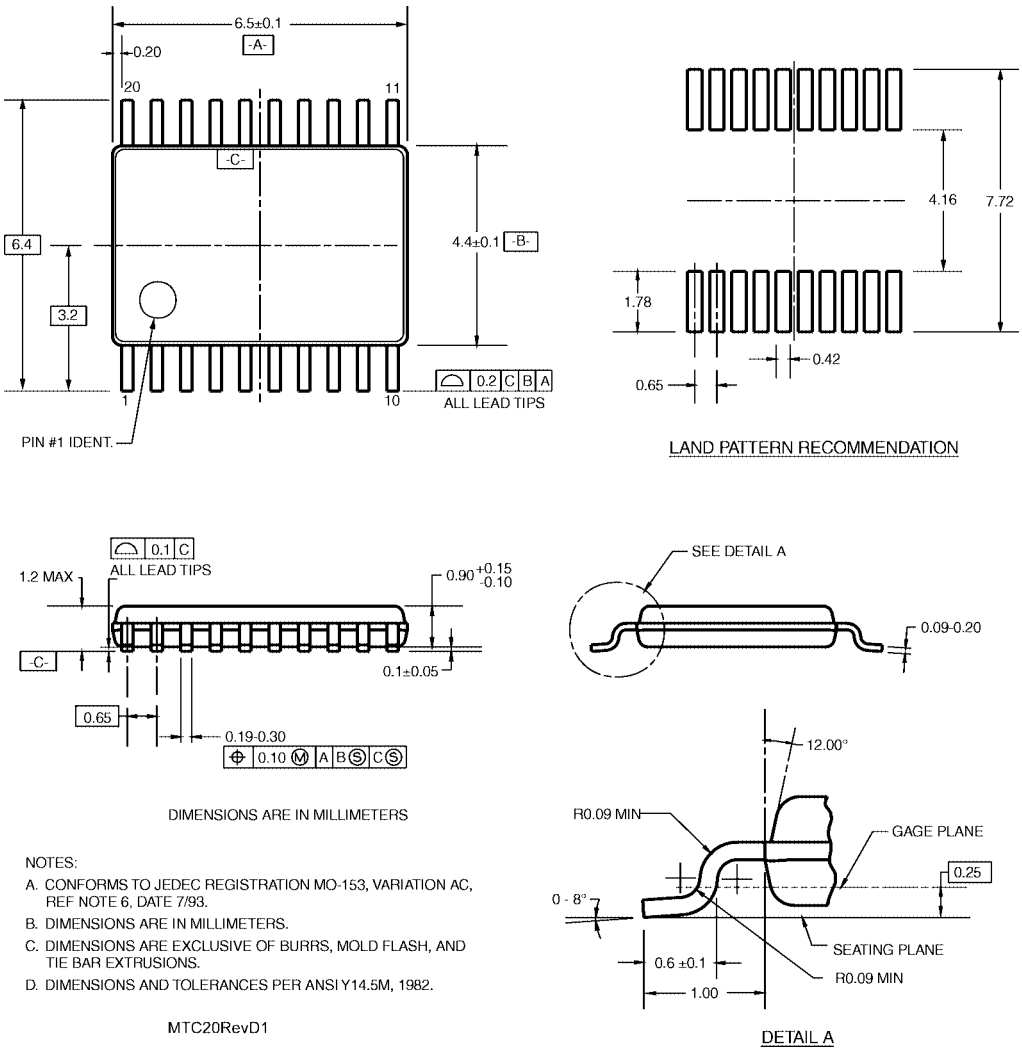
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

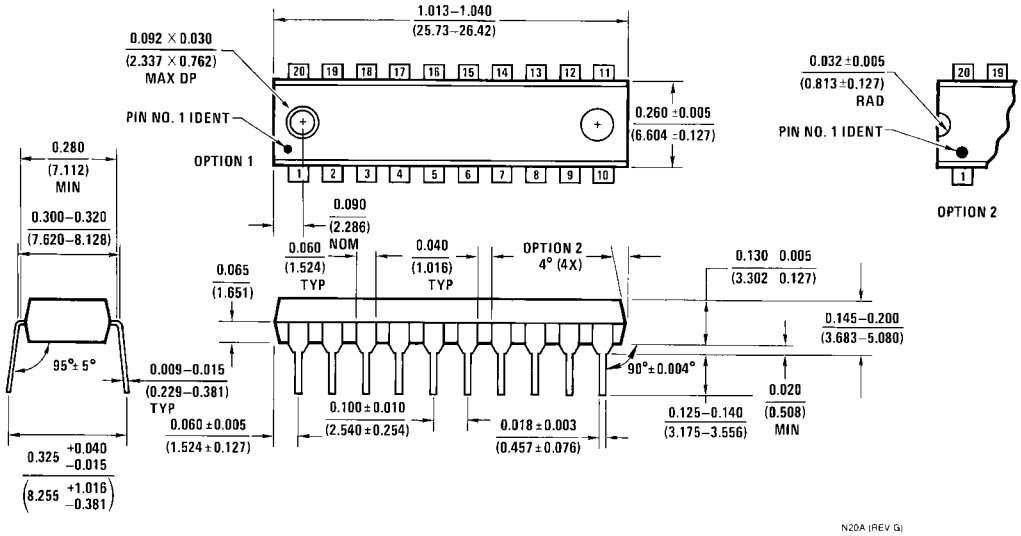
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC32 • 74ACT32
Quad 2-Input OR Gate

General Description

The AC/ACT32 contains four, 2-input OR gates.

Features

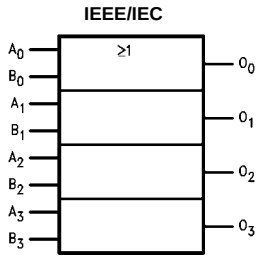
- I_{CC} reduced by 50% on 74AC only
- Outputs source/sink 24 mA
- ACT32 has TTL-compatible inputs

Ordering Code:

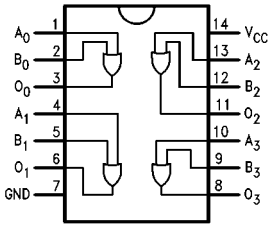
Order Number	Package Number	Package Description
74AC32SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC32PC	N14A	14-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-001, 0.300" Wide
74ACT32SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT32PC	N14A	14-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	7.0	9.0	1.5	10.0	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t_{PHL}	Propagation Delay	3.3	1.5	7.0	8.5	1.0	9.0	ns
		5.0	1.5	5.0	7.0	1.0	7.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

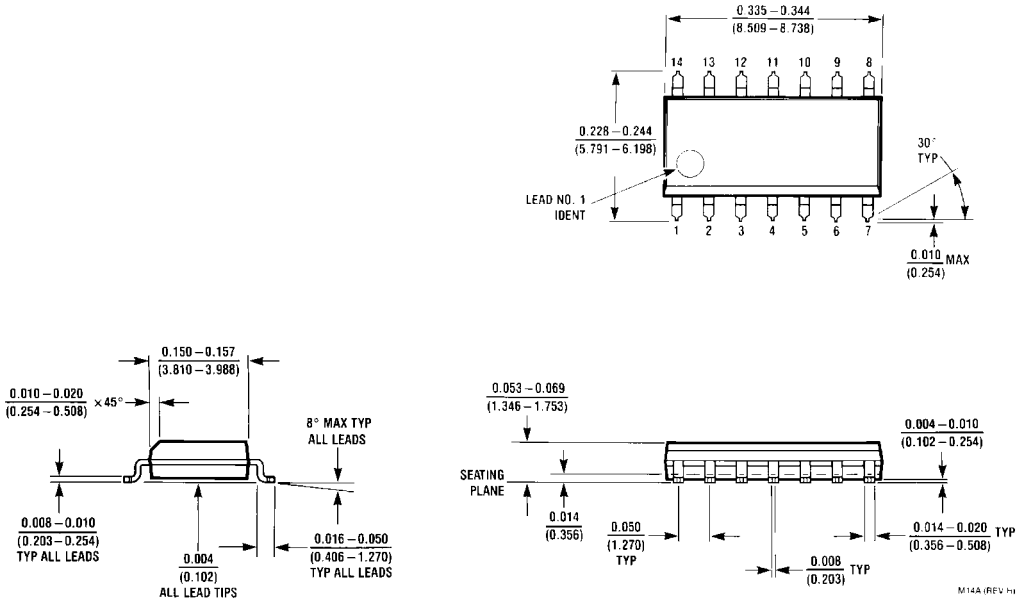
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns
t_{PHL}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.3V

Capacitance

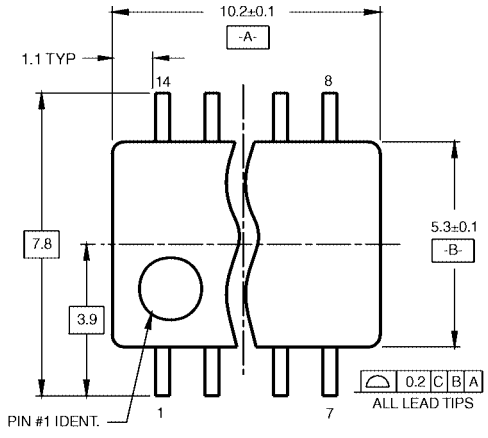
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	20.0	pF	$V_{CC} = 5.0V$

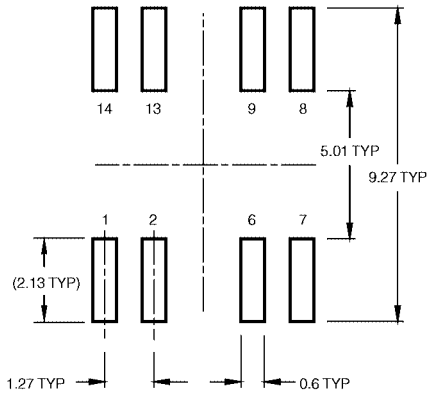
Physical Dimensions inches (millimeters) unless otherwise noted



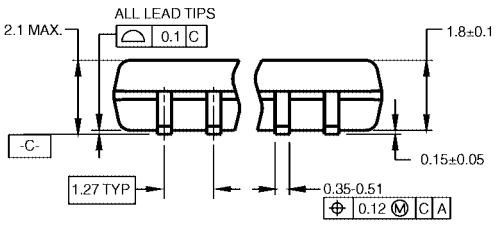
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

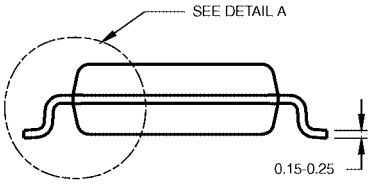
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



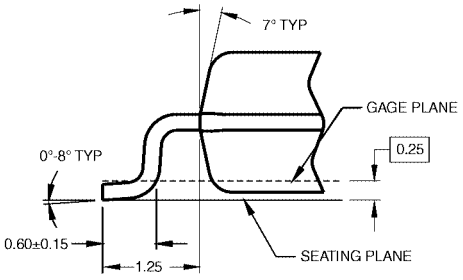


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

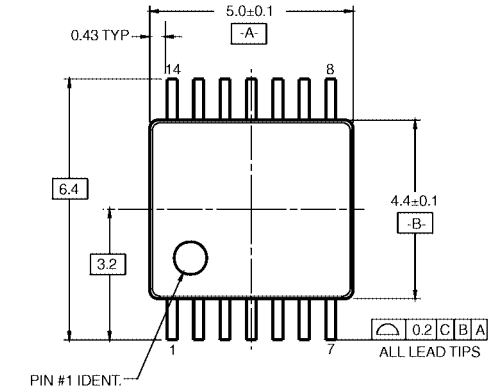
B. DIMENSIONS ARE IN MILLIMETERS.

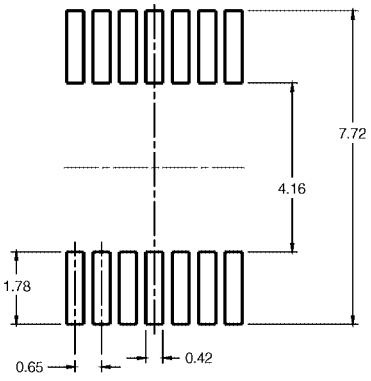
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

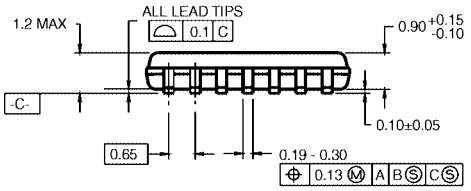
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

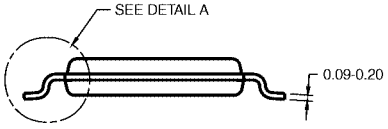
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

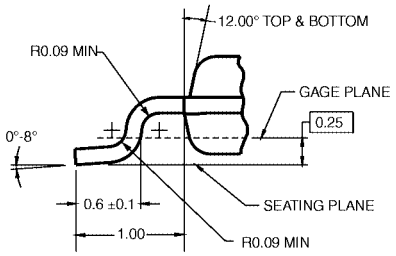




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

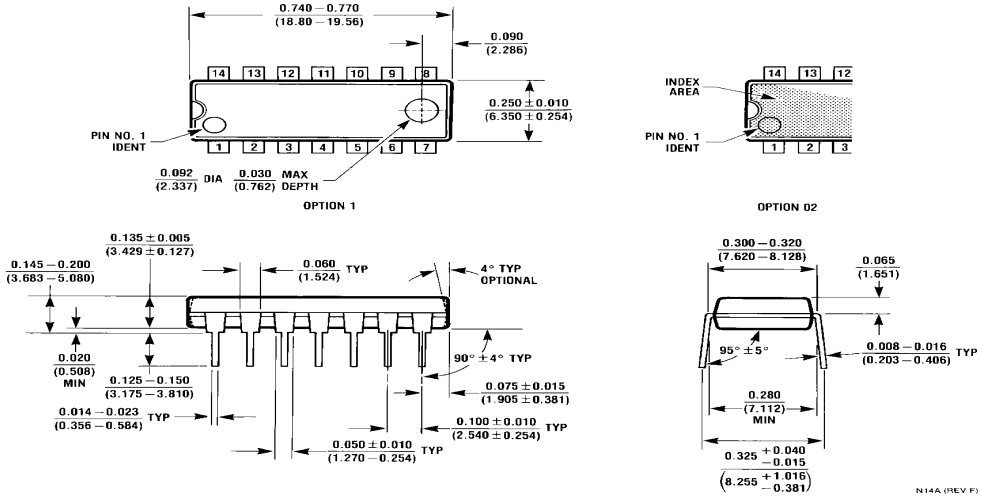
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-001, 0.300” Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC373 • 74ACT373
Octal Transparent Latch with 3-STATE Outputs

General Description

The AC/ACT373 consists of eight latches with 3-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state.

Features

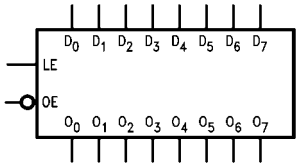
- I_{CC} and I_{OZ} reduced by 50%
- Eight latches in a single package
- 3-STATE outputs for bus interfacing
- Outputs source/sink 24 mA
- ACT373 has TTL-compatible inputs

Ordering Code:

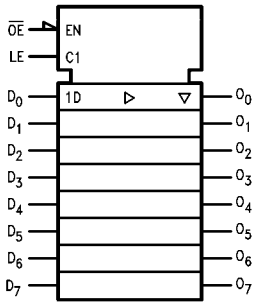
Order Number	Package Number	Package Description
74AC373SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC373PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT373SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT373MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACT373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT373PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering information

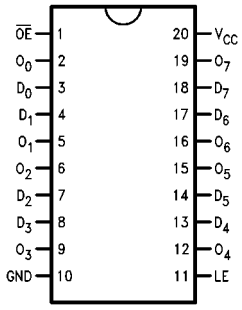
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

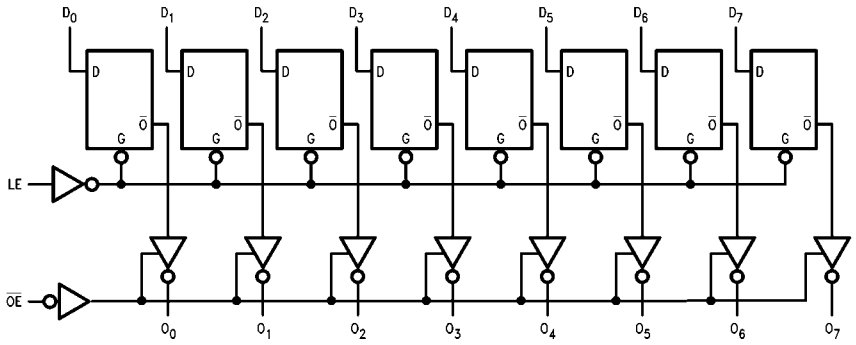
The AC/ACT373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW, the latches store the information that was present on the D-type inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OL} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	± 2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded, thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		± 0.25	± 2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay D_n to O_n	3.3	1.5	10.0	13.5	1.5	15.0	ns
		5.0	1.5	7.0	9.5	1.5	10.5	
t_{PHL}	Propagation Delay D_n to O_n	3.3	1.5	9.5	13.0	1.5	14.5	ns
		5.0	1.5	7.0	9.5	1.5	10.5	
t_{PLH}	Propagation Delay LE to O_n	3.3	1.5	10.0	13.5	1.5	15.0	ns
		5.0	1.5	7.5	9.5	1.5	10.5	
t_{PHL}	Propagation Delay LE to O_n	3.3	1.5	9.5	12.5	1.5	14.0	ns
		5.0	1.5	7.0	9.5	1.5	10.5	
t_{PZH}	Output Enable Time	3.3	1.5	9.0	11.5	1.0	13.0	ns
		5.0	1.5	7.0	8.5	1.0	9.5	
t_{PZL}	Output Enable Time	3.3	1.5	8.5	11.5	1.0	13.0	ns
		5.0	1.5	6.5	8.5	1.0	9.5	
t_{PHZ}	Output Disable Time	3.3	1.5	10.0	12.5	1.0	14.5	ns
		5.0	1.5	8.0	11.0	1.0	12.5	
t_{PLZ}	Output Disable Time	3.3	1.5	8.0	11.5	1.0	12.5	ns
		5.0	1.5	6.5	8.5	1.0	10.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	3.5	5.5	6.0	ns
	D_n to LE	5.0	2.0	4.0	4.5	
t_H	Hold Time, HIGH or LOW	3.3	−3.0	1.0	1.0	ns
	D_n to LE	5.0	−1.5	1.0	1.0	
t_W	LE Pulse Width,	3.3	4.0	5.5	6.0	ns
	HIGH	5.0	2.0	4.0	4.5	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to O_n	5.0	2.5	8.5	10.0	1.5	11.5	ns
t_{PHL}	Propagation Delay D_n to O_n	5.0	2.0	8.0	10.0	1.5	11.5	ns
t_{PLH}	Propagation Delay LE to O_n	5.0	2.5	8.5	11.0	2.0	11.5	ns
t_{PHL}	Propagation Delay LE to O_n	5.0	2.0	8.0	10.0	1.5	11.5	ns
t_{PZH}	Output Enable Time	5.0	2.0	8.0	9.5	1.5	10.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	7.5	9.0	1.5	10.5	ns
t_{PHZ}	Output Disable Time	5.0	2.5	9.0	11.0	2.5	12.5	ns
t_{PLZ}	Output Disable Time	5.0	1.5	7.5	8.5	1.0	10.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

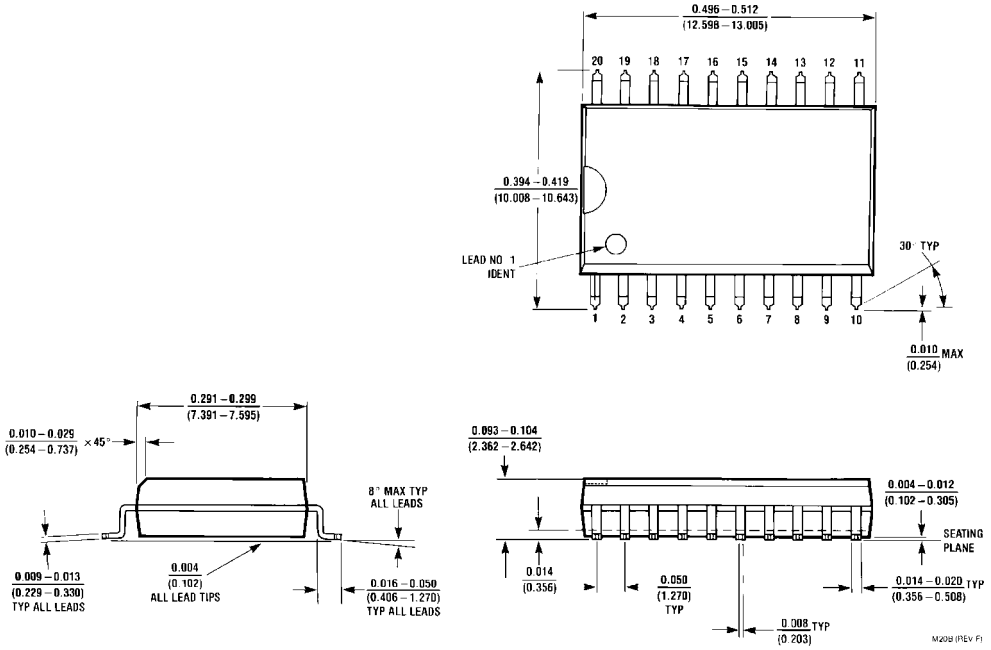
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	0.8	2.5	3.5	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0	0	1.0	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	7.0	8.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

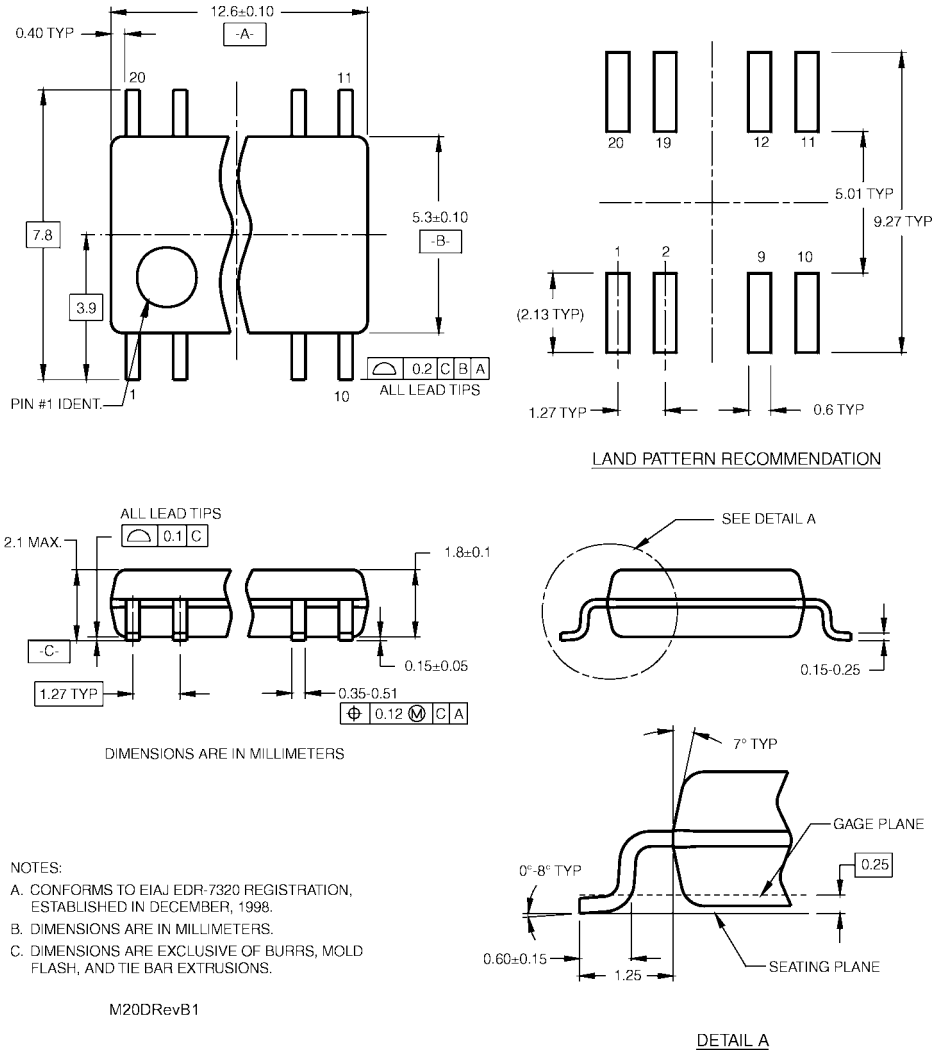
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

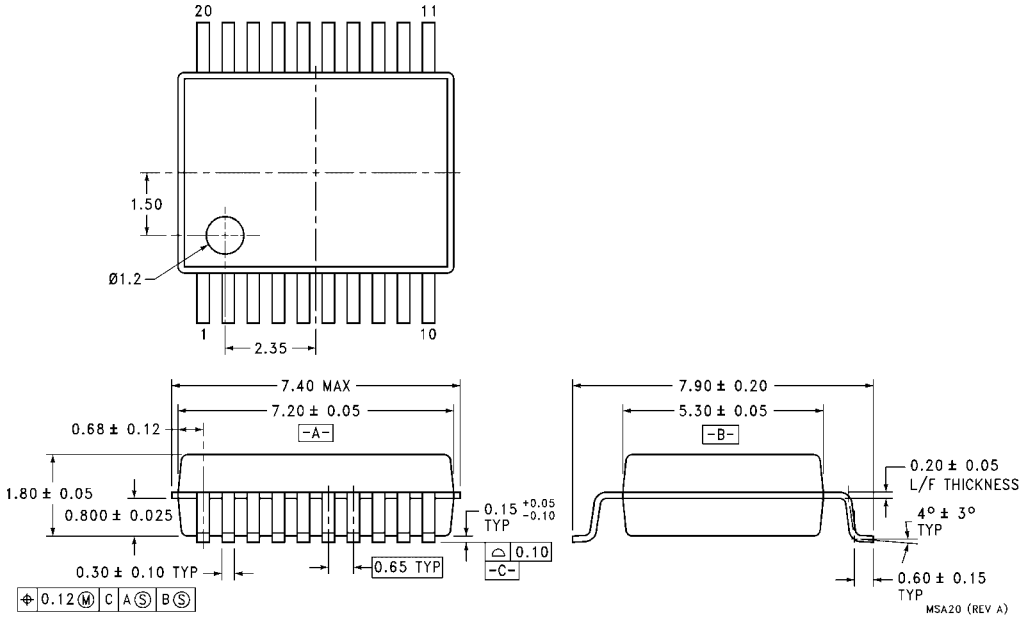
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

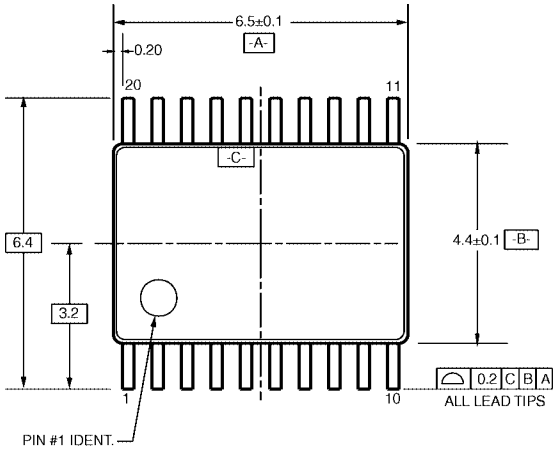
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

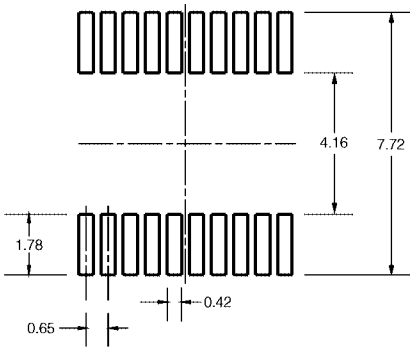
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



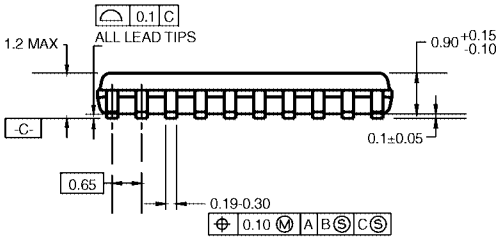
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

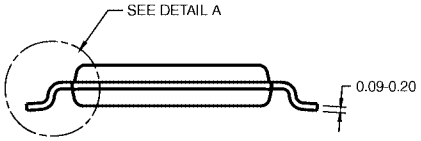
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

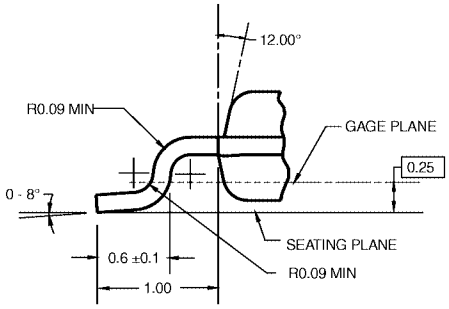
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

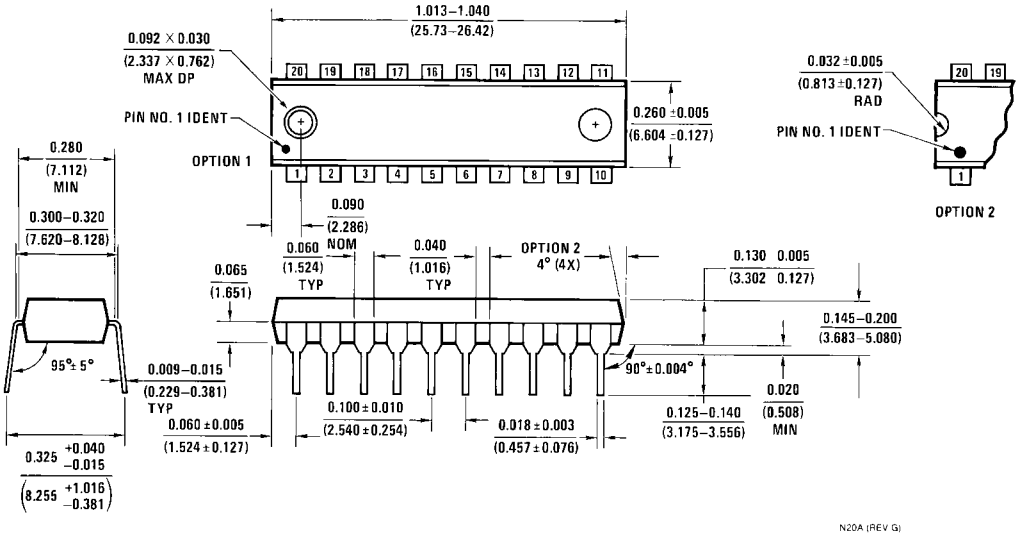
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC374 • 74ACT374
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The AC/ACT374 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

Features

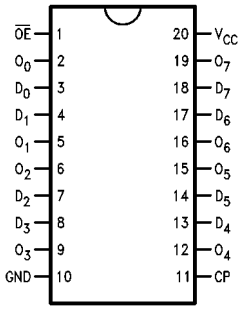
- I_{CC} and I_{OZ} reduced by 50%
- Buffered positive edge-triggered clock
- 3-STATE outputs for bus-oriented applications
- Outputs source/sink 24 mA
- See 273 for reset version
- See 377 for clock enable version
- See 373 for transparent latch version
- See 574 for broadside pinout version
- See 564 for broadside pinout version with inverted outputs
- ACT374 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC374SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74AC374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC374PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT374SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74ACT374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT374MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACT374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT374PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

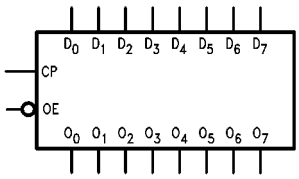


Pin Descriptions

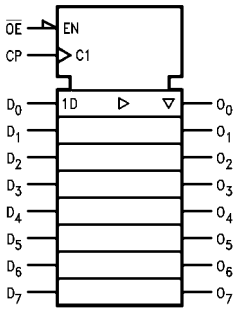
Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC



Functional Description

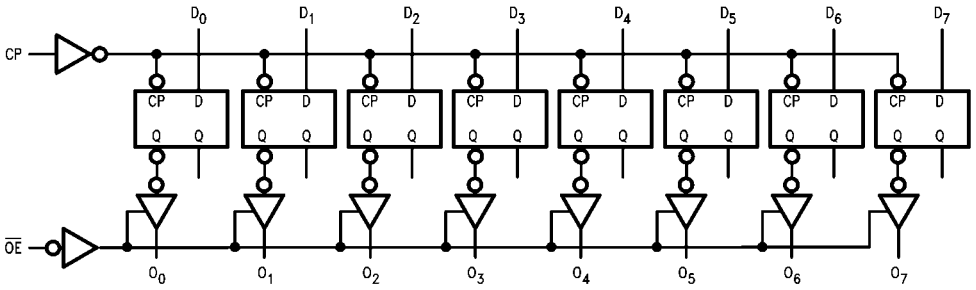
The AC/ACT374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	− 0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	− 20 mA
V_I = V_{CC} + 0.5V	+ 20 mA
DC Input Voltage (V_I)	− 0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = − 0.5V	− 20 mA
V_O = V_{CC} + 0.5V	+ 20 mA
DC Output Voltage (V_O)	− 0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	− 65°C to + 150°C
Junction Temperature (T_J) (PDIP)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = − 50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = − 12 mA
		4.5		3.86	3.76	V	I_{OH} = − 24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current						V_I (OE) = V_{IL}, V_{IH}
		5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} - 24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°$, $CC_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	3.3	60	110		60		MHz
		5.0	100	155		100		
t_{PLH}	Propagation Delay CP to O_n	3.3	3.0	11.0	13.5	1.5	15.5	ns
		5.0	2.5	8.0	9.5	1.5	10.5	
t_{PHL}	Propagation Delay CP to O_n	3.3	2.5	10.0	12.5	2.0	14.0	ns
		5.0	2.0	7.0	9.0	1.5	10.0	
t_{PZH}	Output Enable Time	3.3	3.0	9.5	11.5	1.5	13.0	ns
		5.0	2.0	7.0	8.5	1.0	9.5	
t_{PZL}	Output Enable Time	3.3	2.5	9.0	11.5	1.5	13.0	ns
		5.0	2.0	6.5	8.5	1.0	9.5	
t_{PHZ}	Output Disable Time	3.3	3.0	10.5	12.5	2.0	14.5	ns
		5.0	2.0	8.0	11.0	2.0	12.5	
t_{PLZ}	Output Disable Time	3.3	2.0	8.0	11.5	1.0	12.5	ns
		5.0	1.5	6.5	8.5	1.0	10.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	2.0	5.5	6.0	ns
	D_n to CP	5.0	1.0	4.0	4.5	
t_H	Hold Time, HIGH or LOW	3.3	−1.0	1.0	1.0	ns
	D_n to CP	5.0	0	1.5	1.5	
t_W	CP Pulse Width,	3.3	4.0	5.5	6.0	ns
	HIGH or LOW	5.0	2.5	4.0	4.5	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	100	160		90		MHz
t_{PLH}	Propagation Delay CP to O_n	5.0	2.0	8.5	10.0	2.0	11.5	ns
t_{PHL}	Propagation Delay CP to O_n	5.0	2.0	8.0	9.5	1.5	11.0	ns
t_{PZH}	Output Enable Time	5.0	2.0	8.0	9.5	1.5	10.5	ns
t_{PZL}	Output Enable Time	5.0	1.5	8.0	9.0	1.5	10.5	ns
t_{PHZ}	Output Disable Time	5.0	1.5	8.5	11.5	1.0	12.5	ns
t_{PLZ}	Output Disable Time	5.0	1.5	7.0	8.5	1.0	10.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements

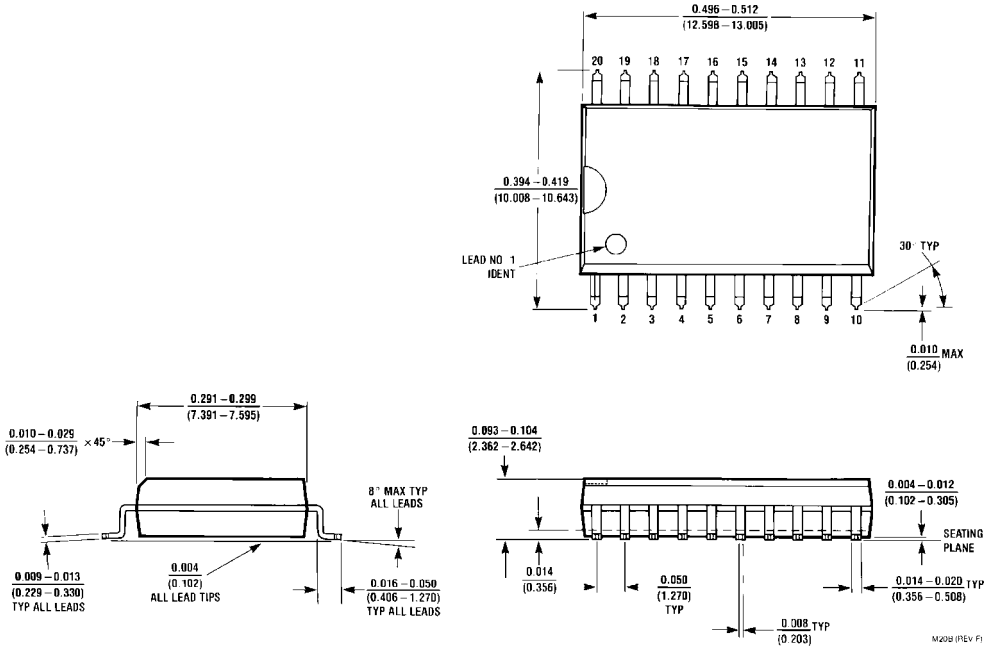
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	1.0	5.5	5.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	1.5	1.5	ns
t_W	CP Pulse Width, HIGH or LOW	5.0	2.5	5.0	5.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

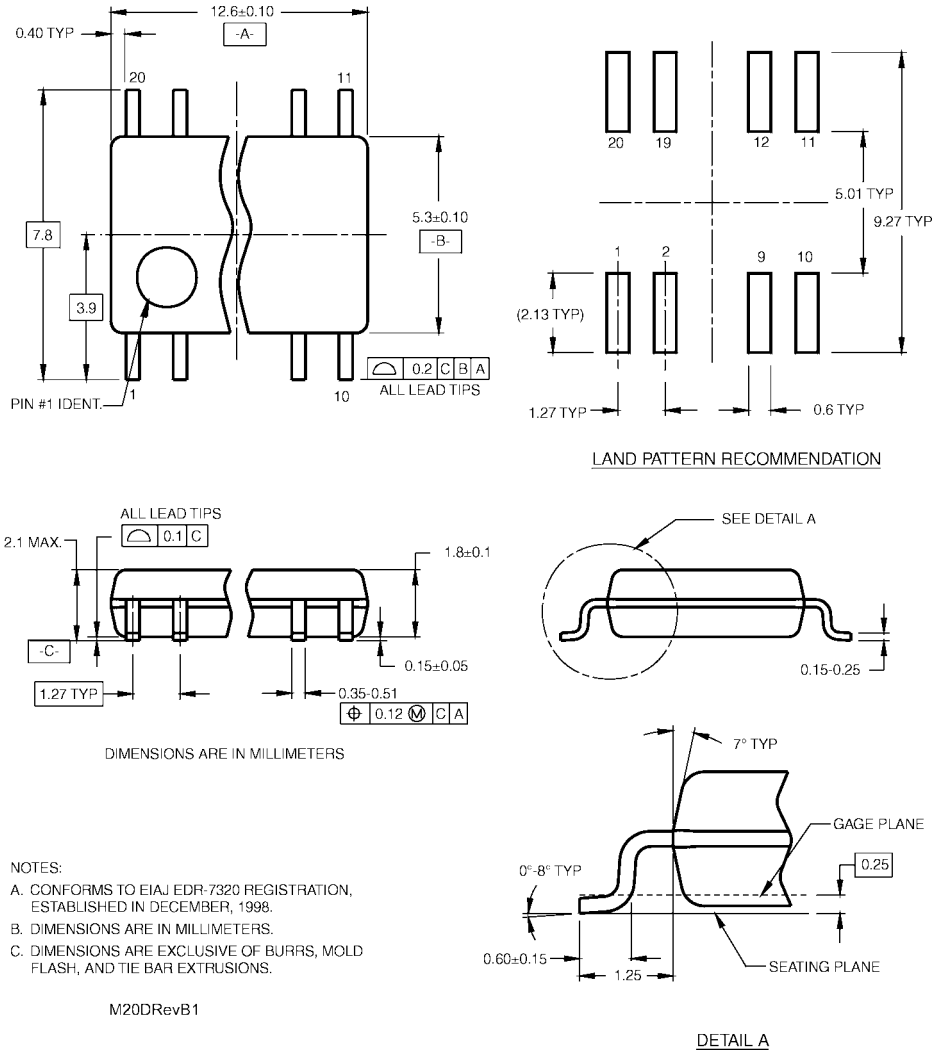
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

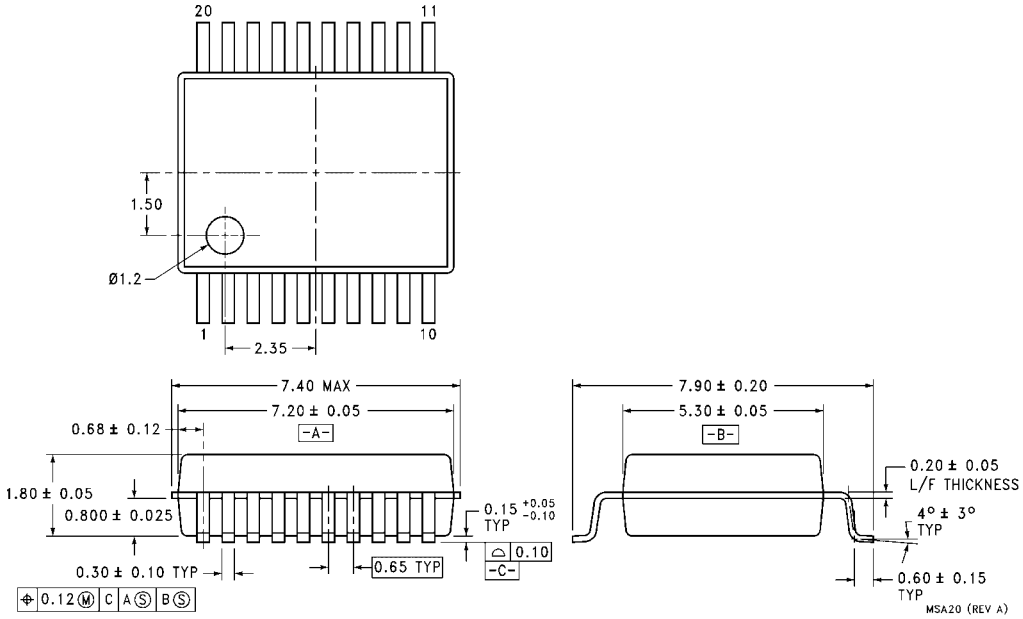
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

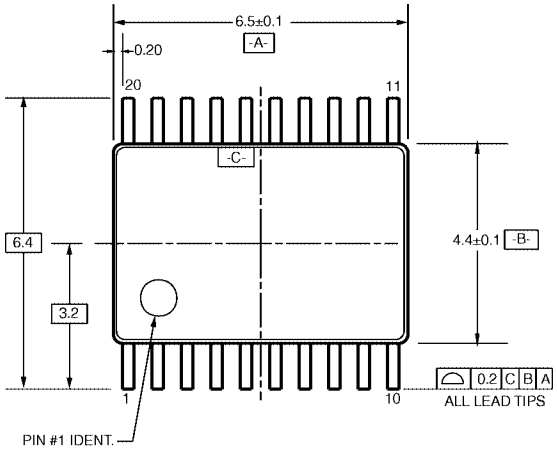
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

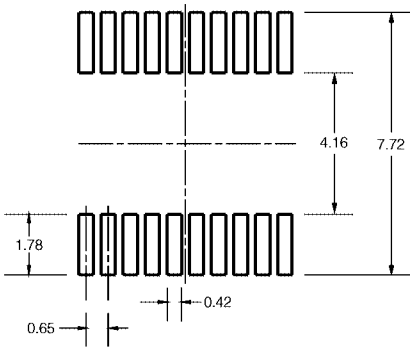
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



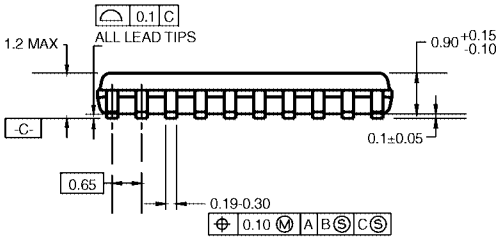
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

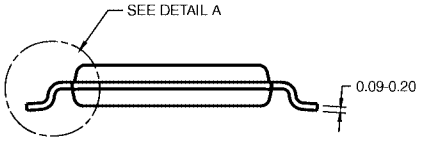
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

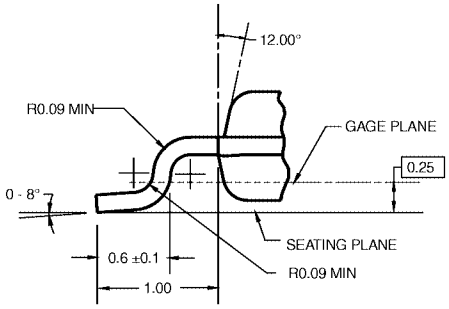
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

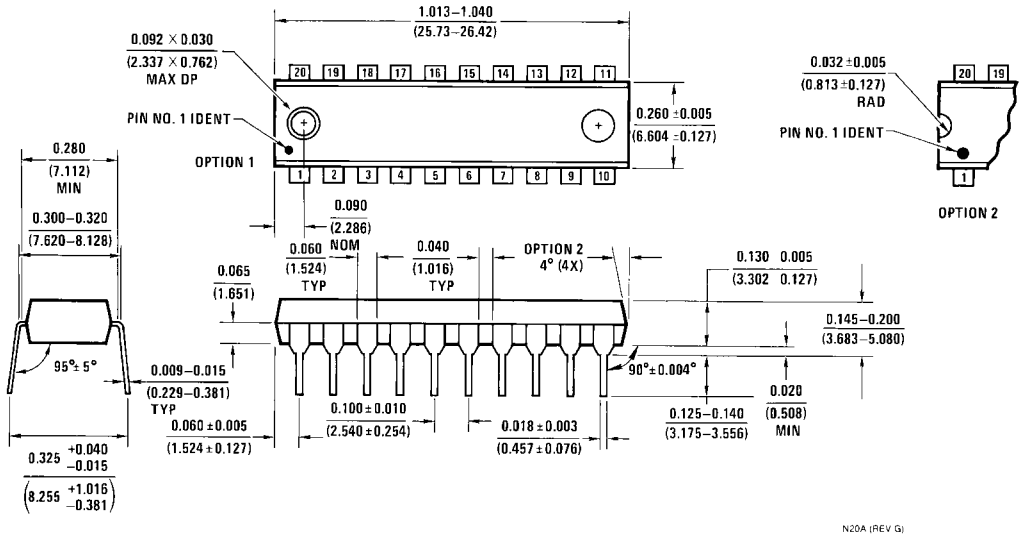
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-in-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC377 • 74ACT377
Octal D-Type Flip-Flop with Clock Enable

General Description

The AC/ACT377 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) input loads all flip-flops simultaneously, when the Clock Enable ($\overline{CE}$) is LOW.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output. The $\overline{CE}$ input must be stable only one setup time prior to the LOW-to-HIGH clock transition for predictable operation.

Features

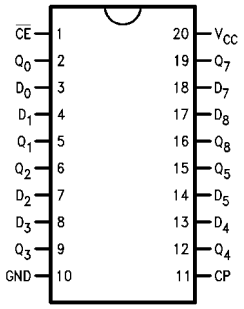
- I_{CC} reduced by 50%
- Ideal for addressable register applications
- Clock enable for address and data synchronization applications
- Eight edge-triggered D-type flip-flops
- Buffered common clock
- Outputs source/sink 24 mA
- See 273 for master reset version
- See 373 for transparent latch version
- See 374 for 3-STATE version
- ACT377 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC377SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC377SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC377MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC377PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT377SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT377SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT377MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT377PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

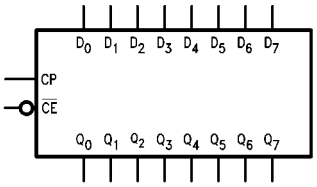


Pin Descriptions

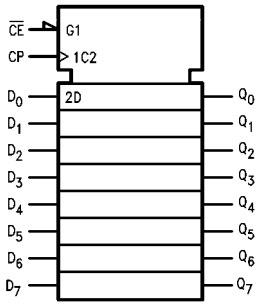
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{CE}$	Clock Enable (Active LOW)
Q_0–Q_7	Data Outputs
CP	Clock Pulse Input

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC

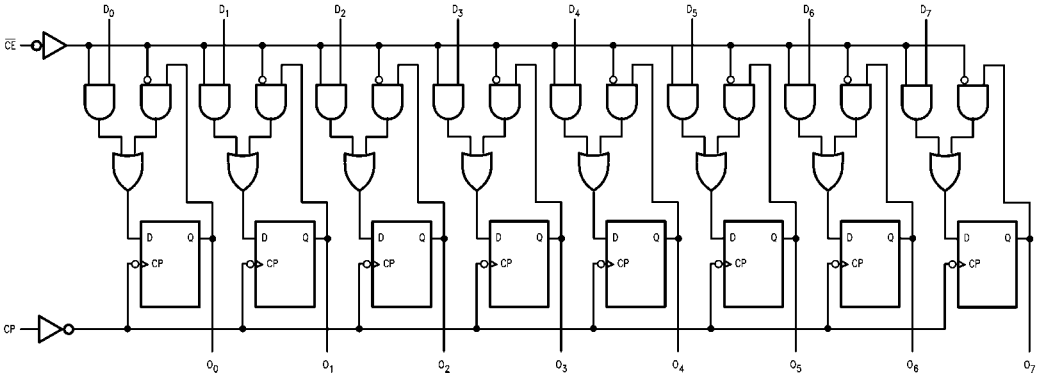


Mode Select-Function Table

Operating Mode	Inputs			Outputs
	CP	$\overline{CE}$	D_n	Q_n
Load '1'	⌐	L	H	H
Load '0'	⌐	L	L	L
Hold (Do Nothing)	⌐	H	X	No Change
	X	H	X	No Change

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	2.0	2.0		or $V_{CC} - 0.1V$
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	0.8	0.8		or $V_{CC} - 0.1V$
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
	Output Voltage	5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
	Output Voltage	5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock	3.3	90	125		75		MHz
	Frequency	5.0	140	175		125		
t_{PLH}	Propagation Delay	3.3	3.0	8.0	13.0	1.5	14.0	ns
	CP to Q_n	5.0	2.0	6.0	9.0	1.5	10.0	
t_{PHL}	Propagation Delay	3.3	3.5	8.5	13.0	2.0	14.5	ns
	CP to Q_n	5.0	2.5	6.5	10.0	1.5	11.0	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	3.5	5.5	6.0	ns
	D_n to CP	5.0	2.5	4.0	4.5	
t_H	Hold Time, HIGH or LOW	3.3	−2.0	0	0	ns
	D_n to CP	5.0	−1.0	1.0	1.0	
t_S	Setup Time, HIGH or LOW	3.3	4.0	6.0	7.5	ns
	$\overline{CE}$ to CP	5.0	2.5	4.0	4.5	
t_H	Hold Time, HIGH or LOW	3.3	−3.5	0	0	ns
	$\overline{CE}$ to CP	5.0	−2.0	1.0	1.0	
t_W	CP Pulse Width	3.3	3.5	5.5	6.0	ns
	HIGH or LOW	5.0	2.5	4.0	4.5	

Note 8: Voltage Range 3.3 is 3.0V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	140	175		125		MHz
t_{PLH}	Propagation Delay CP to Q_n	5.0	3.0	6.5	9.0	2.5	10.0	ns
t_{PHL}	Propagation Delay CP to Q_n	5.0	3.5	7.0	10.0	2.5	11.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

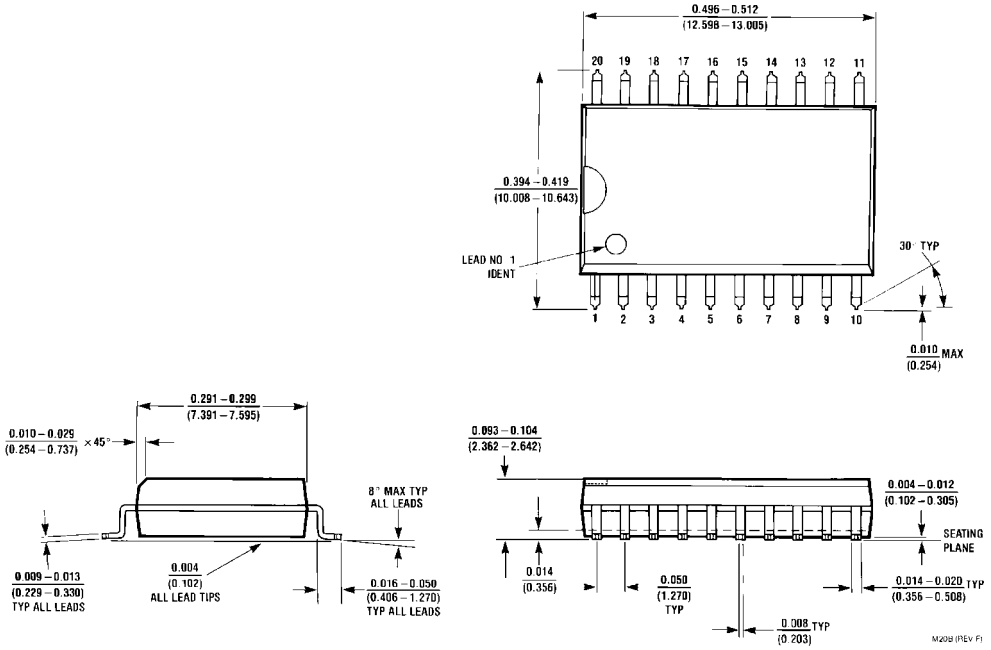
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	2.5	4.5	5.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	−1.0	1.0	1.0	ns
t_S	Setup Time, HIGH or LOW $\overline{CE}$ to CP	5.0	2.5	4.5	5.5	ns
t_H	Hold Time, HIGH or LOW $\overline{CE}$ to CP	5.0	−1.0	1.0	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.0	4.0	4.5	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

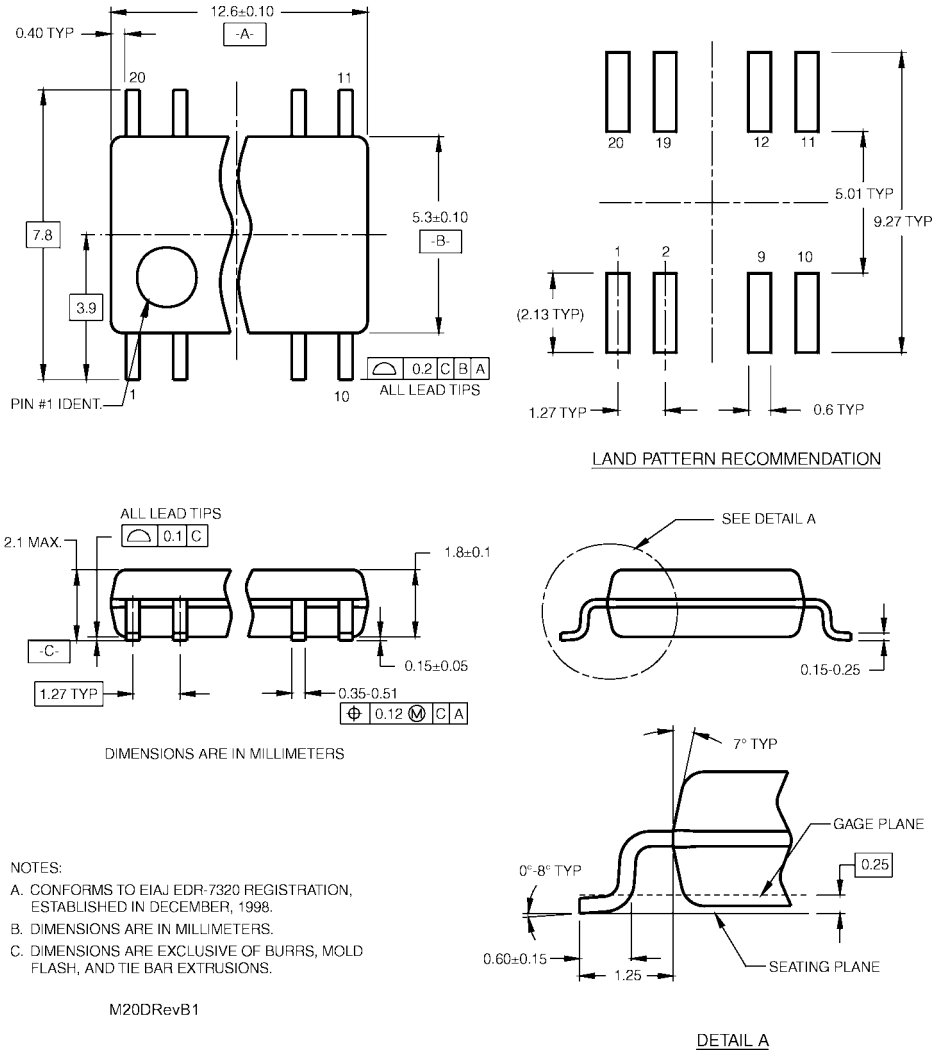
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	90.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

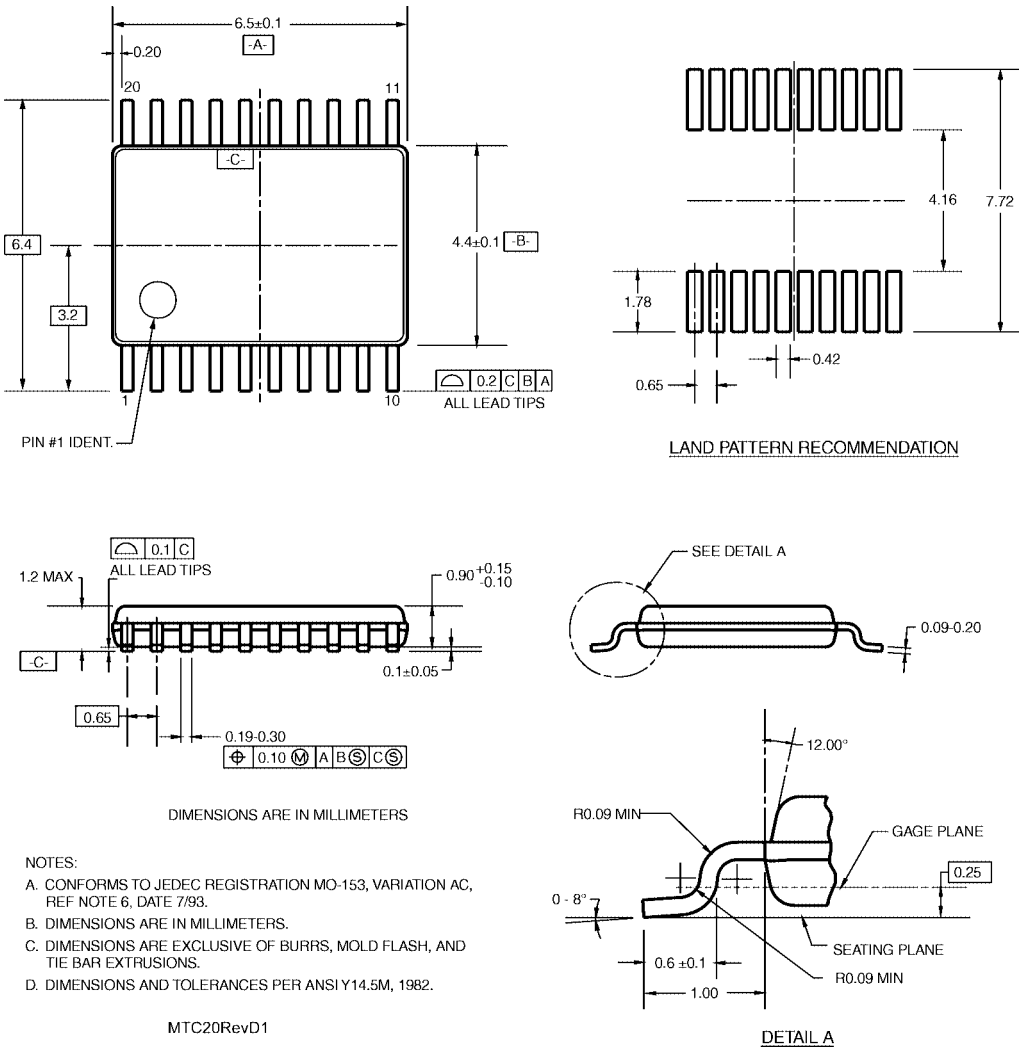
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

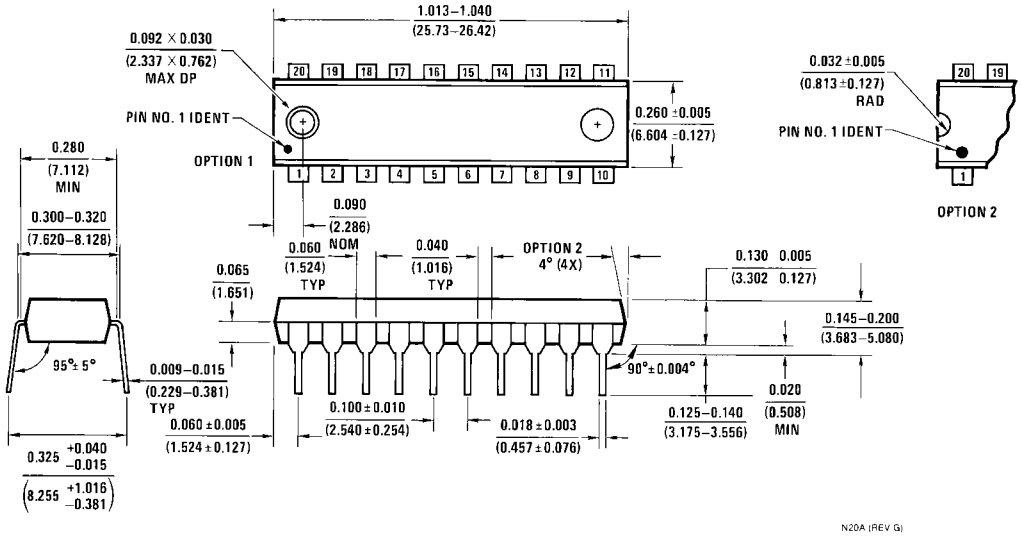
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

June 1988
Revised November 1999

74AC399 • 74ACT399
Quad 2-Port Register

General Description

The AC/ACT399 is the logical equivalent of a quad 2-input multiplexer feeding into four edge-triggered flip-flops. A common Select input determines which of the two 4-bit words is accepted. The selected data enters the flip-flop on the rising edge of the clock.

Features

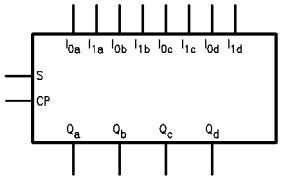
- I_{CC} reduced by 50%
- Select inputs from two data sources
- Fully positive edge-triggered operation
- Outputs source/sink 24 mA
- AC/ACT399 has TTL-compatible inputs

Ordering Code:

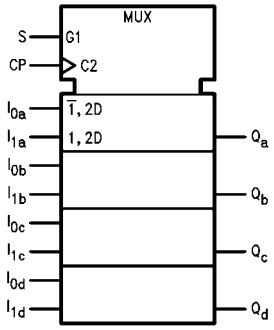
Order Number	Package Number	Package Description
74AC399SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74AC399PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACT399SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74ACT399SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT399PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

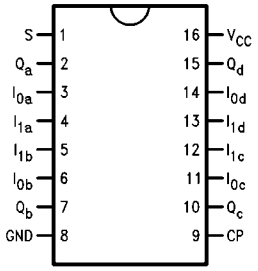
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
S	Common Select Input
CP	Clock Pulse Input
I_{0a}–I_{0d}	Data Inputs from Source 0
I_{1a}–I_{1d}	Data Inputs from Source 1
Q_a–Q_d	Register True Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

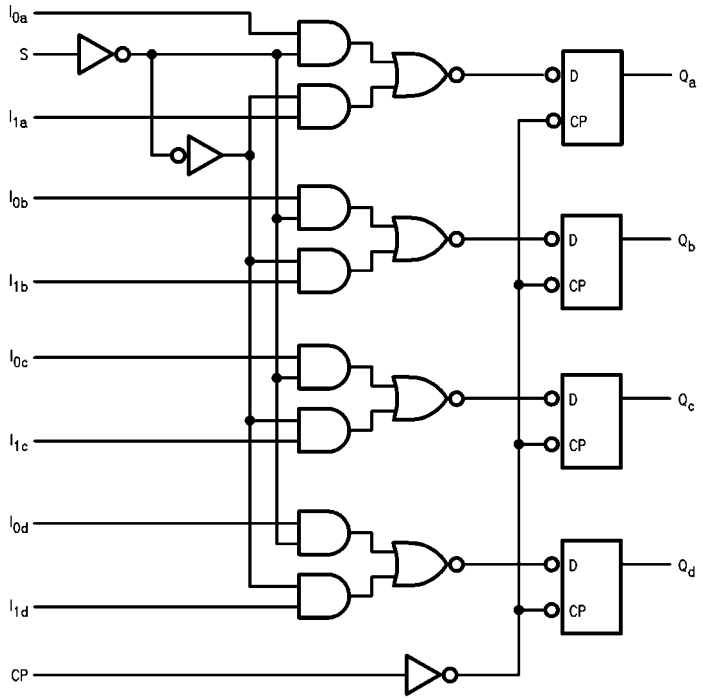
The AC/ACT399 is a high-speed quad 2-port register. It selects four bits of data from either of two sources (Ports) under control of a common Select input (S). The selected data is transferred to a 4-bit output register synchronous with the LOW-to-HIGH transition of the Clock input (CP). The 4-bit D-type output register is fully edge-triggered. The Data inputs (I_{0x}, I_{1x}) and Select input (S) must be stable only a setup time prior to and hold time after the LOW-to-HIGH transition of the Clock input for predictable operation.

Function Table

Inputs				Outputs	
S	**I_0**	**I_1**	**CP**	**Q**	**$\overline{Q}$**
L	L	X	⌐	L	H
L	H	X	⌐	H	L
H	X	L	⌐	L	H
H	X	H	⌐	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	+140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH}= −12 mA
		4.5		3.86	3.76		I_{OH}= −24 mA
		5.5		4.86	4.76		I_{OH}= −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL}= 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.85	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or Ground

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ tp $+85°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Input Clock Frequency	3.3	140	160		130		MHz
		5.0	170	190		165		
t_{PLH}	Propagation Delay CP to Q	3.3	4.0	7.5	10.0	3.5	11.0	ns
		5.0	2.0	5.0	8.0	1.5	8.5	
t_{PHL}	Propagation Delay CP to Q	3.3	3.5	7.0	9.5	3.0	10.5	ns
		5.0	2.0	5.0	7.5	1.5	8.0	

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	2.0	4.0	4.0	ns
	I_n to CP	5.0	1.5	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	0.5	1.0	1.0	ns
	I_n to CP	5.0	0.5	1.0	1.0	
t_S	Setup Time, HIGH or LOW	3.3	3.5	5.5	5.5	ns
	S to CP	5.0	2.0	4.0	4.0	
t_H	Hold Time, HIGH or LOW	3.3	0.5	1.0	1.0	ns
	S to CP	5.0	0.5	1.0	1.0	
t_W	CP Pulse Width,	3.3	3.0	4.5	4.5	ns
	HIGH or LOW	5.0	2.0	3.5	3.5	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $V_{CC} = 5.0V$, $C_L = 50$pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Input Clock Frequency	5.0	165	180		160		MHz
t_{PLH}	Propagation Delay CP to Q	5.0	1.5	7.0	8.0	1.5	8.5	ns
t_{PHL}	Propagation Delay CP to Q	5.0	2.0	6.0	9.0	2.0	9.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

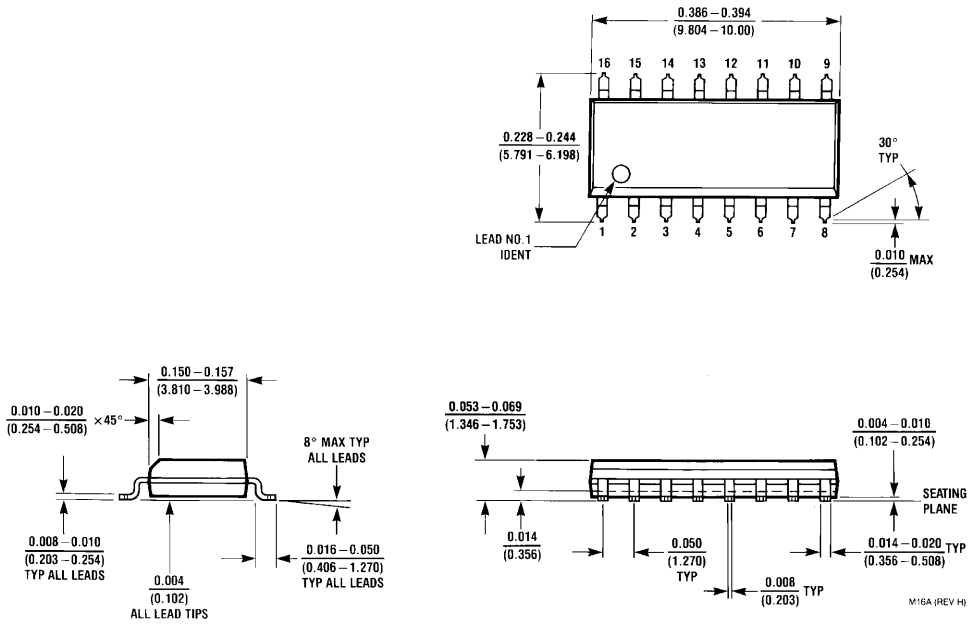
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	5.0	0.8	2.5	2.5	ns
	I_n to CP					
t_H	Hold Time, HIGH or LOW	5.0	0	1.0	1.0	ns
	I_n to CP					
t_S	Setup Time, HIGH or LOW	5.0	0.8	4.0	4.0	ns
	S to CP					
t_H	Hold Time, HIGH or LOW	5.0	−1.0	0.5	0.5	ns
	S to CP					
t_W	CP Pulse Width,	5.0	1.7	3.5	3.5	ns
	HIGH or LOW					

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

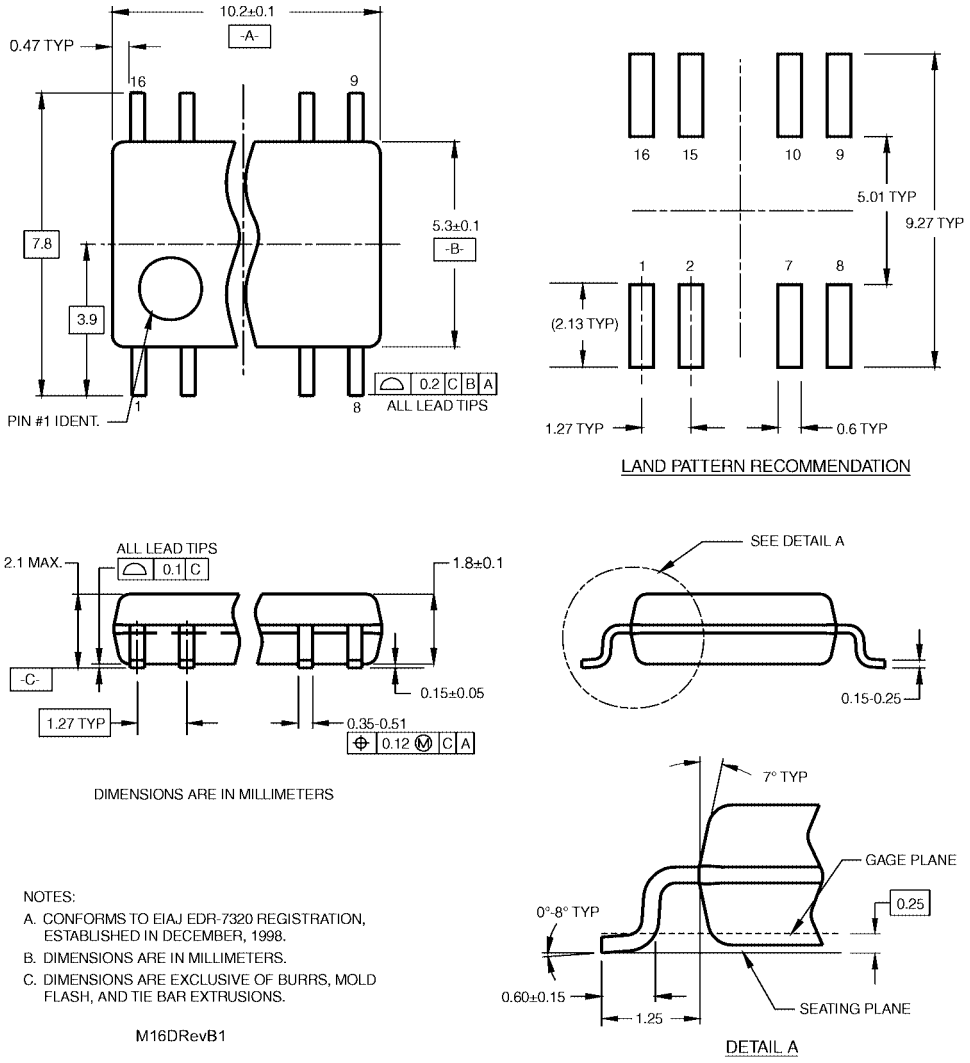
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	30	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

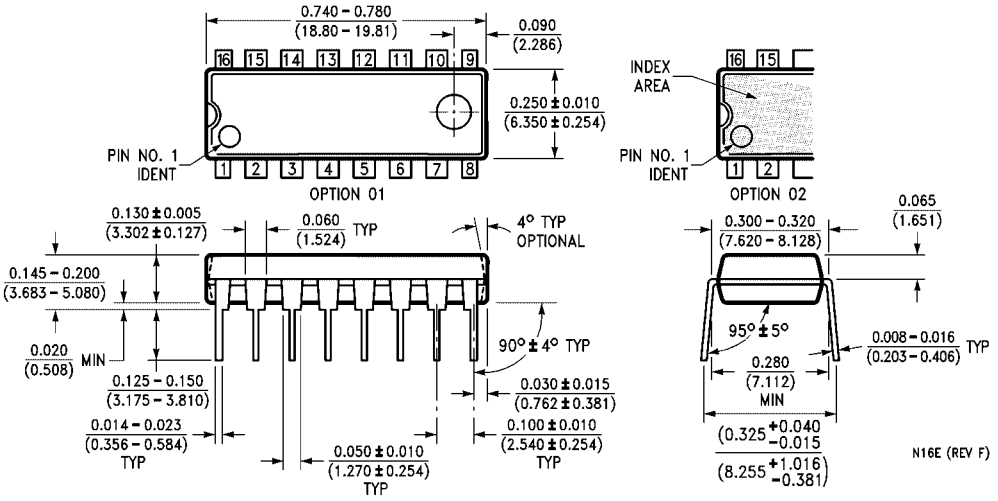
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

February 1989
Revised November 1999

74AC520 • 74ACT520
8-Bit Identity Comparator

General Description

The AC/ACT520 are expandable 8-bit comparators. They compare two words of up to eight bits each and provide a LOW output when the two words match bit for bit. The expansion input $\overline{I}_{A=B}$ also serves as an active LOW enable input.

Features

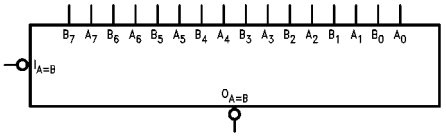
- Compares two 8-bit words in 6.5 ns typ
- Expandable to any word length
- 20-pin package
- Outputs source/sink 24 mA
- ACT520 has TTL-compatible inputs

Ordering Code:

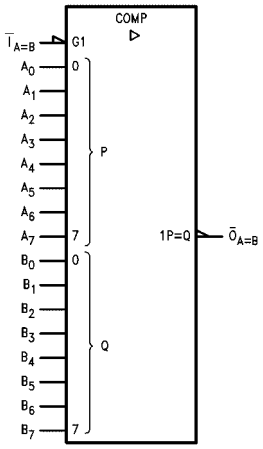
Order Number	Package Number	Package Description
74AC520SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC520PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT520SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT520SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT520PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

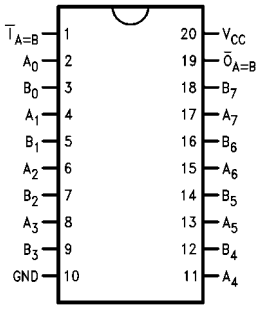
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7	Word A Inputs
B_0–B_7	Word B Inputs
$T_{A=B}$	Expansion or Enable Input
$\overline{O}_{A=B}$	Identity Output

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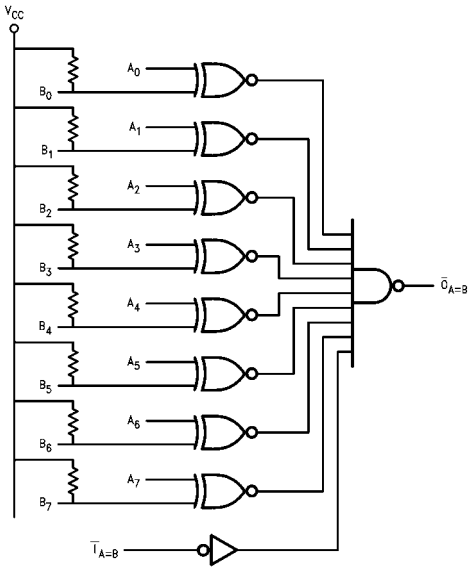
Truth Table

Inputs		Outputs
$\overline{I}_{A=B}$	A, B	$\overline{O}_{A=B}$
L	A = B (Note 1)	L
L	A ≠ B	H
H	A = B (Note 1)	H
H	A ≠ B	H

H = HIGH Voltage Level
L = LOW Voltage Level

Note 1: *$A_0 = B_0$, $A_1 = B_1$, $A_2 = B_2$, etc.

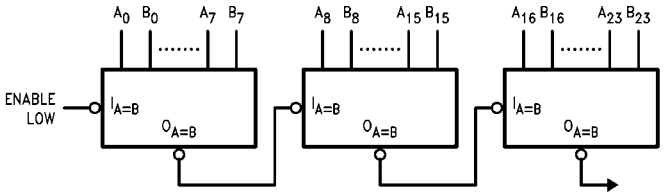
Logic Diagram



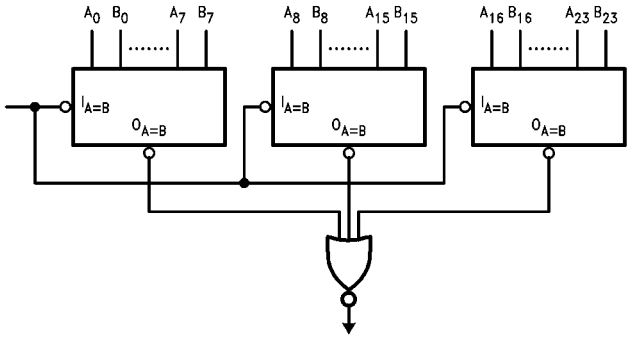
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Applications

Ripple Expansion



Parallel Expansion



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{IN} (Note 5)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND, A Inputs Only
I_{IH}	Maximum Input HIGH Leakage Current	5.5		10.0	10.0	μA	V_I = V_{CC}, B Inputs Only
I_{IL}	Maximum Input LOW Leakage Current	5.5	−0.3	−0.6	−1.0	mA	V_I = V_{CC}, B Inputs Only
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC}
I_{CC} (Note 5)	Maximum Quiescent Supply Current	5.5	2.3	4.8	8.0	mA	V_{IN} = GND

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 6)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 6)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{IH}	Maximum Input HIGH Leakage Current	5.5		10.0	10.0	μA	$V_I = V_{CC}$ B Inputs Only
I_{IL}	Maximum Input LOW Leakage Current	5.5	−0.3	−0.6	−1.0	mA	$V_I = V_{CC}$ B Inputs Only
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 7)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND
I_{CC}	Maximum Quiescent Supply Current	5.5	2.3	4.8	8.0	mA	V_{IN} = GND

Note 6: All outputs loaded; thresholds on input associated with output under test.

Note 7: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	4.0	7.5	11.5	3.0	13.0	ns
	A_n or B_n to $\overline{O}_{A=B}$	5.0	2.5	5.5	8.5	2.0	9.5	
t_{PHL}	Propagation Delay	3.3	4.5	8.0	12.0	3.5	13.5	ns
	A_n or B_n to $\overline{O}_{A=B}$	5.0	3.0	5.5	9.0	2.5	10.0	
t_{PLH}	Propagation Delay	3.3	3.5	5.5	8.5	2.5	9.5	ns
	$\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	5.0	2.5	4.5	6.5	2.0	7.0	
t_{PHL}	Propagation Delay	3.3	3.5	5.5	8.5	2.5	9.5	ns
	$\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	5.0	2.5	4.5	6.5	2.0	7.0	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

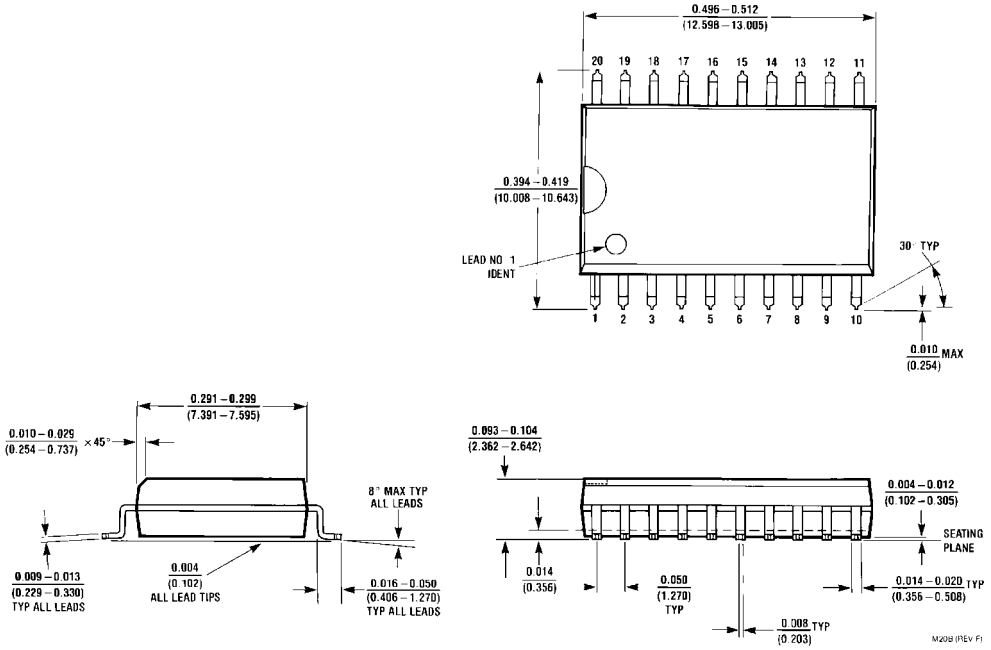
Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay A_n or B_n to $\overline{O}_{A=B}$	5.0	3.0	5.5	8.5	2.5	9.5	ns
t_{PHL}	Propagation Delay A_n or B_n to $\overline{O}_{A=B}$	5.0	3.0	6.0	10.0	2.5	11.5	ns
t_{PLH}	Propagation Delay $\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	5.0	2.0	4.0	6.0	2.0	6.5	ns
t_{PHL}	Propagation Delay $\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	5.0	2.5	5.0	7.5	2.0	8.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

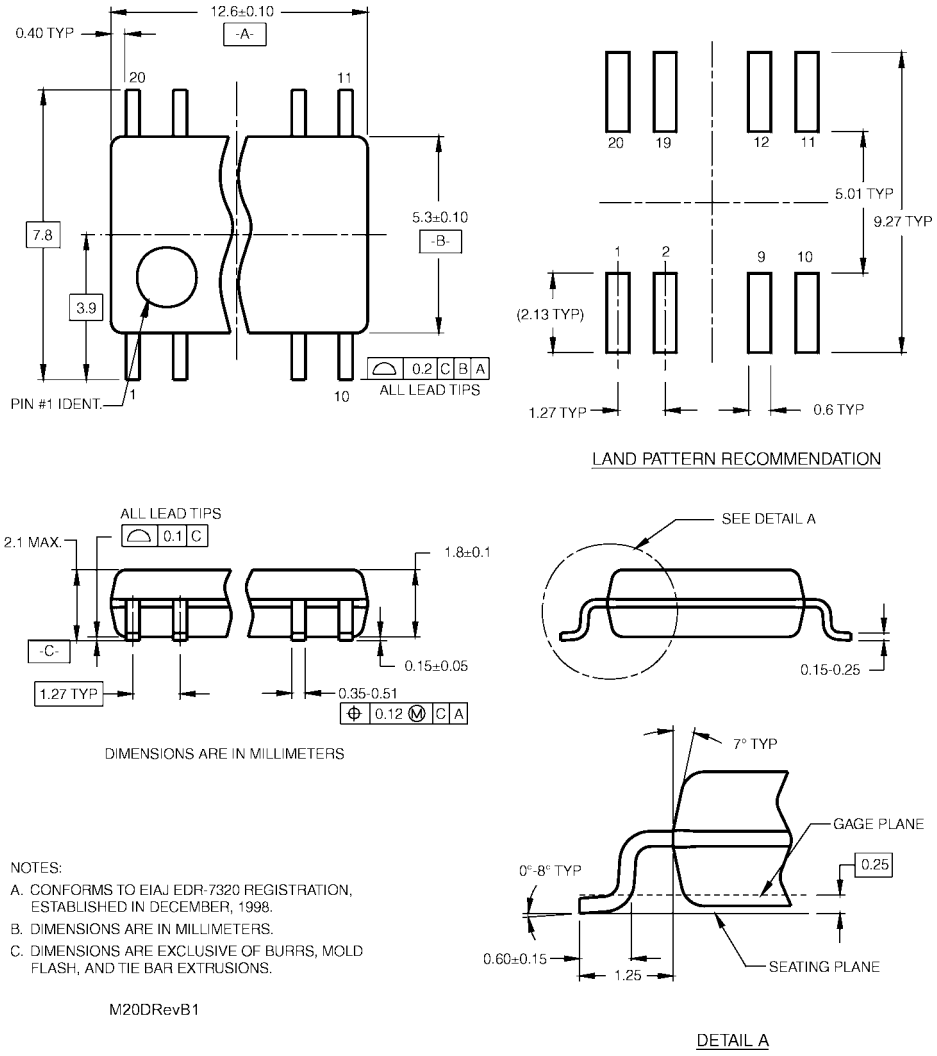
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

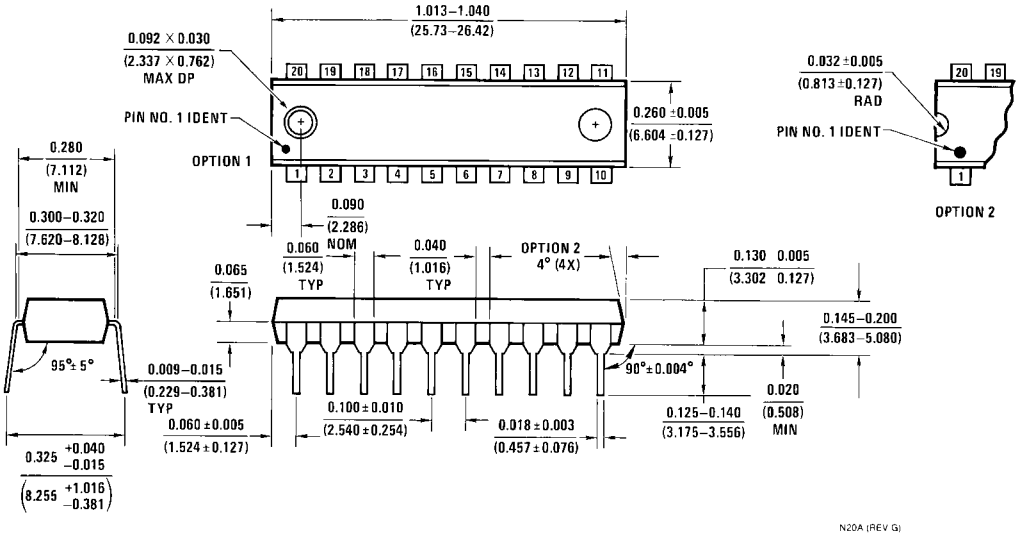
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC521 • 74ACT521
8-Bit Identity Comparator

General Description

The AC/ACT521 is an expandable 8-bit comparator. It compares two words of up to eight bits each and provides a LOW output when the two words match bit for bit. The expansion input $\overline{I}_{A=B}$ also serves as an active LOW enable input.

Features

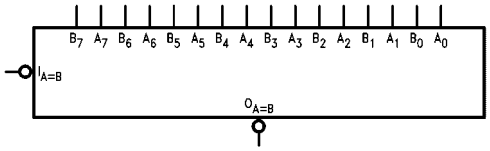
- I_{CC} reduced by 50%
- Compares two 8-bit words in 6.5 ns typ
- Expandable to any word length
- 20-pin package
- Outputs source/sink 24 mA
- ACT521 has TTL-compatible inputs

Ordering Code:

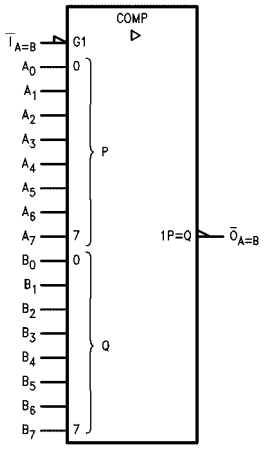
Order Number	Package Number	Package Description
74AC521SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC521SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC521PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT521SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT521SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT521PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering table.

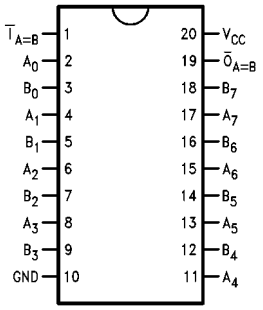
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7	Word A Inputs
B_0–B_7	Word B Inputs
$T_{A=B}$	Expansion or Enable Input
$\overline{O}_{A=B}$	Identity Output

FACT™ is a trademark of Fairchild Semiconductor Corporation.

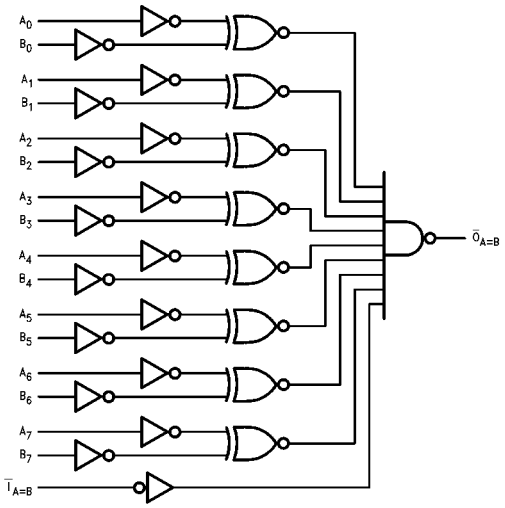
Truth Table

Inputs		Outputs
$\overline{I}_{A=B}$	A, B	$\overline{O}_{A=B}$
L	A = B (Note 1)	L
L	A ≠ B	H
H	A = B (Note 1)	H
H	A ≠ B	H

H = HIGH Voltage Level
L = LOW Voltage Level

Note 1: $A_0 = B_0$, $A_1 = B_1$, $A_2 = B_2$, etc.

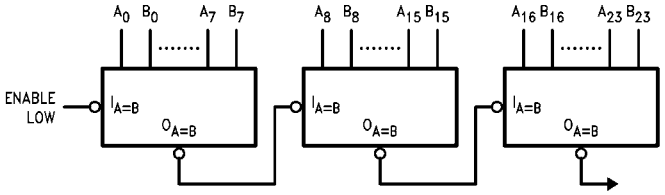
Logic Diagram



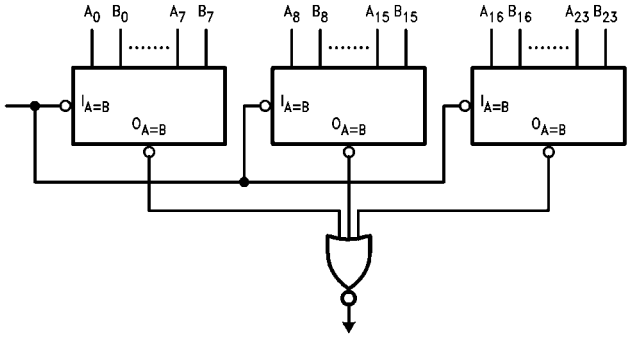
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Applications

Ripple Expansion



Parallel Expansion



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = –0.5V	–20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	–0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = –0.5V	–20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	–0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	–65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	–40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = –40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} – 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} – 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = –50 µA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = –12 mA
		4.5		3.86	3.76	V	I_{OH} = –24 mA
		5.5		4.86	4.76		I_{OH} = –24 mA (Note 3)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{IN} (Note 5)	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			–75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 5)	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	V_{IN} = V_{CC} or GND

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 6)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 6)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 7)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 6: All outputs loaded; thresholds on input associated with output under test.

Note 7: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay A_n or B_n to $\overline{O}_{A=B}$	3.3	3.5	7.0	11.0	3.0	12.0	ns
		5.0	2.5	5.0	8.0	2.0	9.0	
t_{PHL}	Propagation Delay A_n or B_n to $\overline{O}_{A=B}$	3.3	4.5	7.5	11.5	3.5	12.5	ns
		5.0	3.0	5.5	8.5	2.5	9.0	
t_{PLH}	Propagation Delay $\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	3.3	3.0	5.5	8.0	2.5	9.0	ns
		5.0	2.5	4.0	6.0	2.0	7.0	
t_{PHL}	Propagation Delay $\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	3.3	3.0	5.5	8.0	2.5	9.0	ns
		5.0	2.0	4.0	6.0	2.0	7.0	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

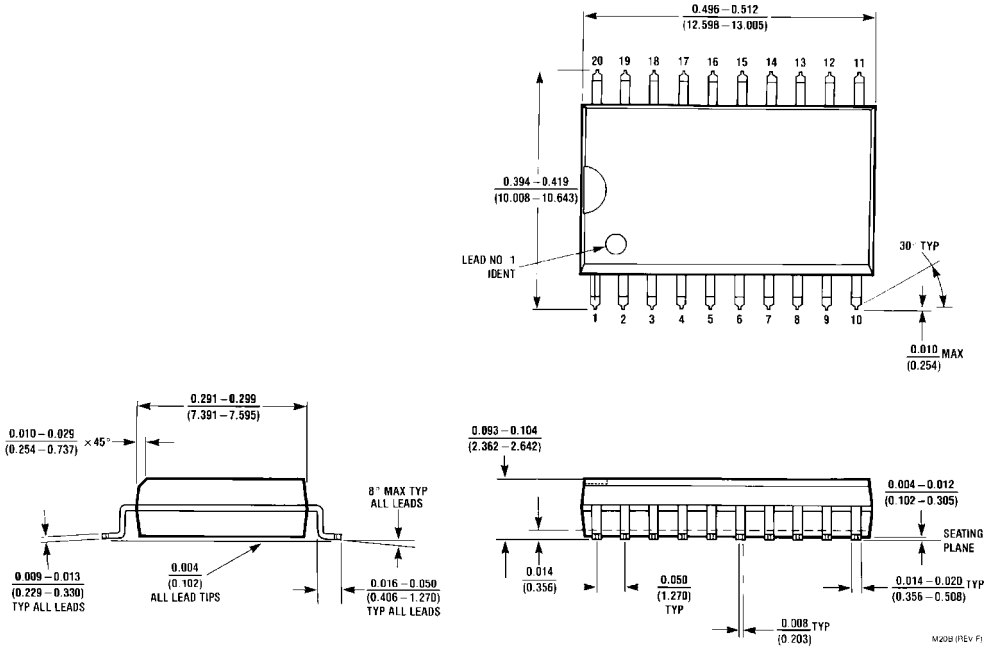
Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay A_n or B_n to $\overline{O}_{A=B}$	5.0	3.0	5.5	9.0	2.5	9.5	ns
t_{PHL}	Propagation Delay A_n or B_n to $\overline{O}_{A=B}$	5.0	3.0	6.0	10.0	2.5	11.0	ns
t_{PLH}	Propagation Delay $\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	5.0	2.0	4.0	6.5	2.0	7.0	ns
t_{PHL}	Propagation Delay $\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	5.0	2.5	5.0	7.5	2.0	8.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

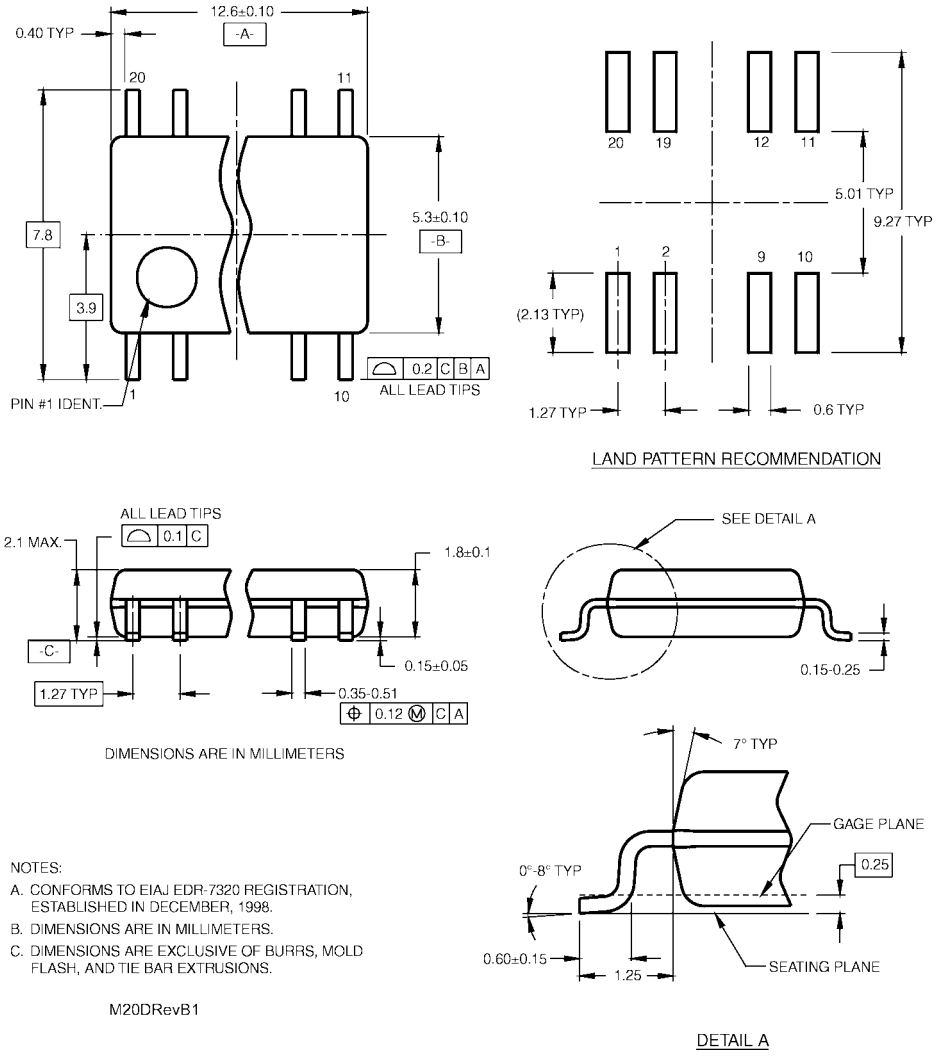
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

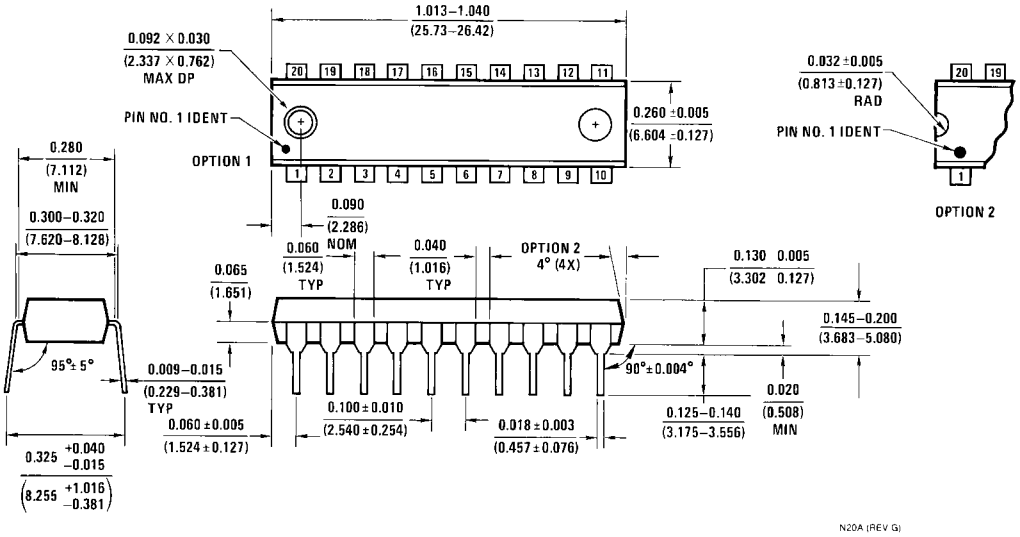
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC540
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The AC540 is an octal buffer/line drivers designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

These devices are similar in function to the AC240 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes these devices especially useful as output ports for microprocessors, allowing ease of layout and greater PC board density.

Features

- I_{CC} and I_{OZ} reduced by 50%
- 3-STATE inverting outputs
- Inputs and outputs opposite side of package, allowing easier interface to microprocessors
- Output source/sink 24 mA

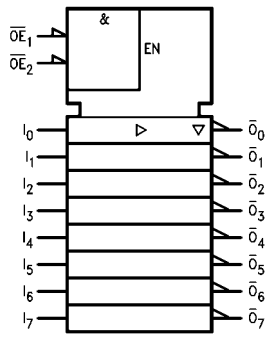
Ordering Code:

Order Number	Package Number	Package Description
74AC540SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC540SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC540MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC540PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

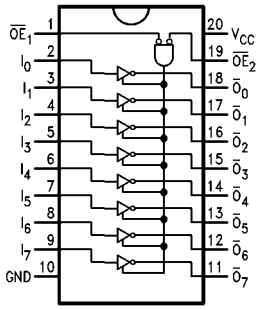
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40° C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

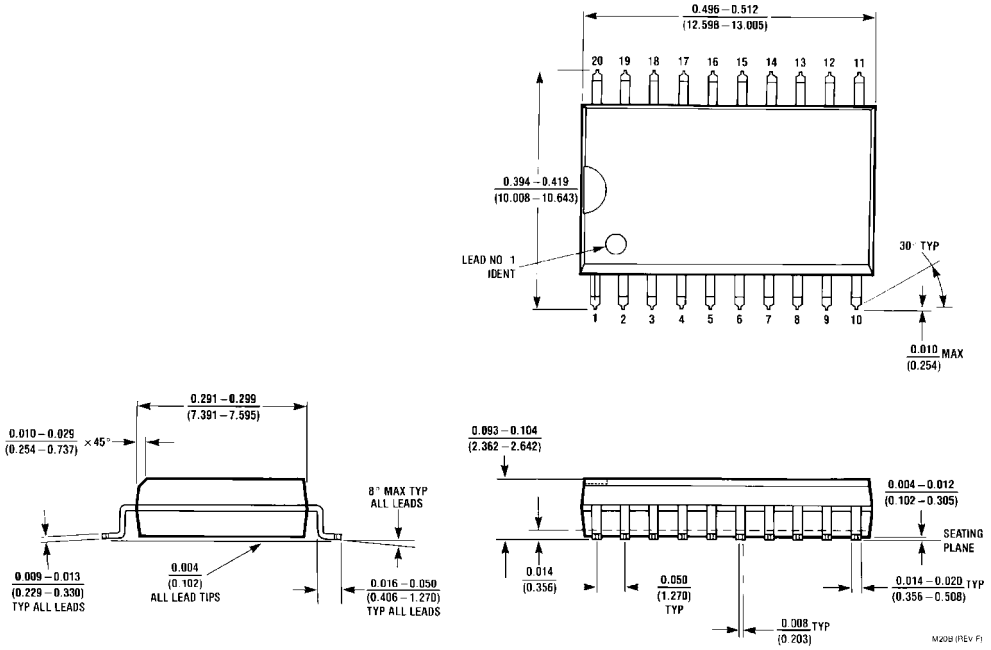
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	5.5	7.5	1.0	8.0	ns
	Data to Output	5.0	1.5	4.0	6.0	1.0	6.5	
t_{PHL}	Propagation Delay	3.3	1.5	5.0	7.0	1.0	7.5	ns
	Data to Output	5.0	1.5	4.0	5.5	1.0	6.0	
t_{PZH}	Output Enable Time	3.3	3.0	8.5	11.0	2.5	12.0	ns
		5.0	2.0	6.5	8.5	2.0	9.5	
t_{PZL}	Output Enable Time	3.3	2.5	7.5	10.0	2.0	11.0	ns
		5.0	2.0	6.0	7.5	1.5	8.5	
t_{PHZ}	Output Disable Time	3.3	2.5	8.5	13.0	1.5	14.0	ns
		5.0	1.5	7.5	10.5	1.0	11.0	
t_{PLZ}	Output Disable Time	3.3	2.5	7.0	10.0	2.0	11.0	ns
		5.0	1.5	6.0	8.0	1.5	9.0	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

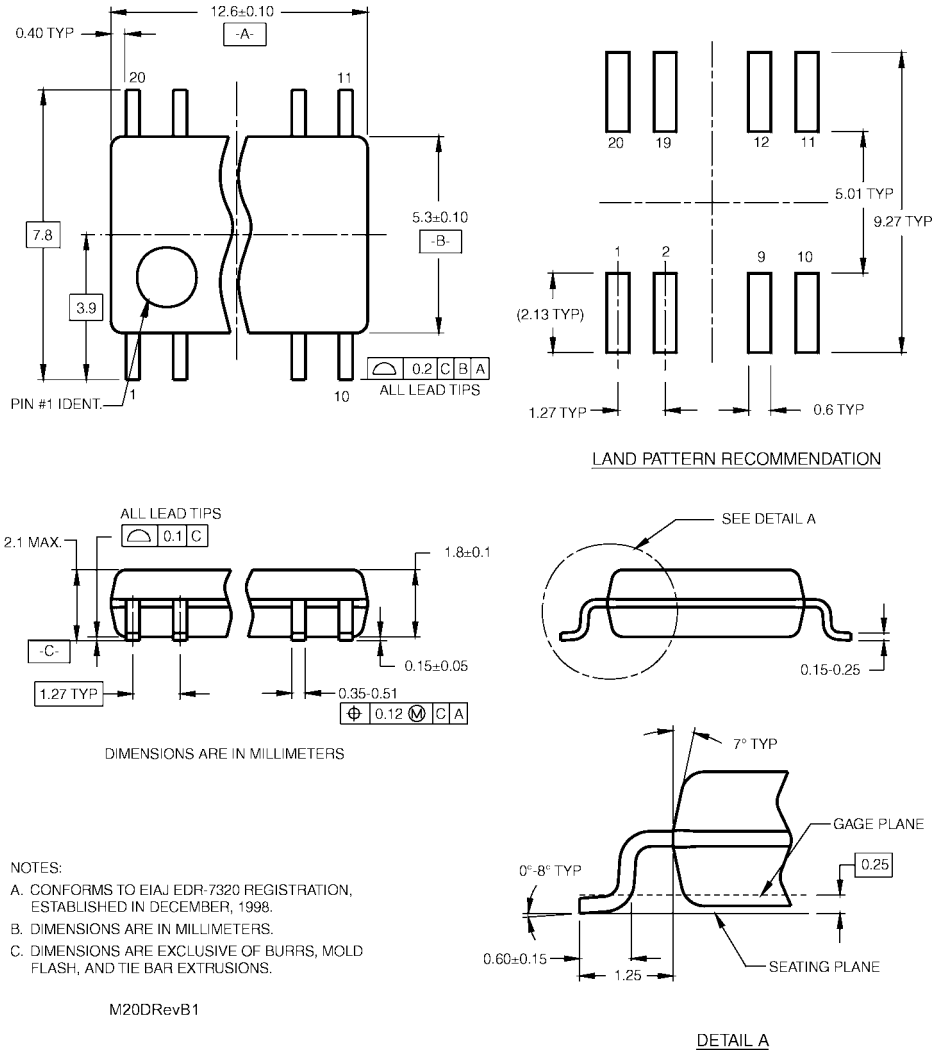
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	30.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

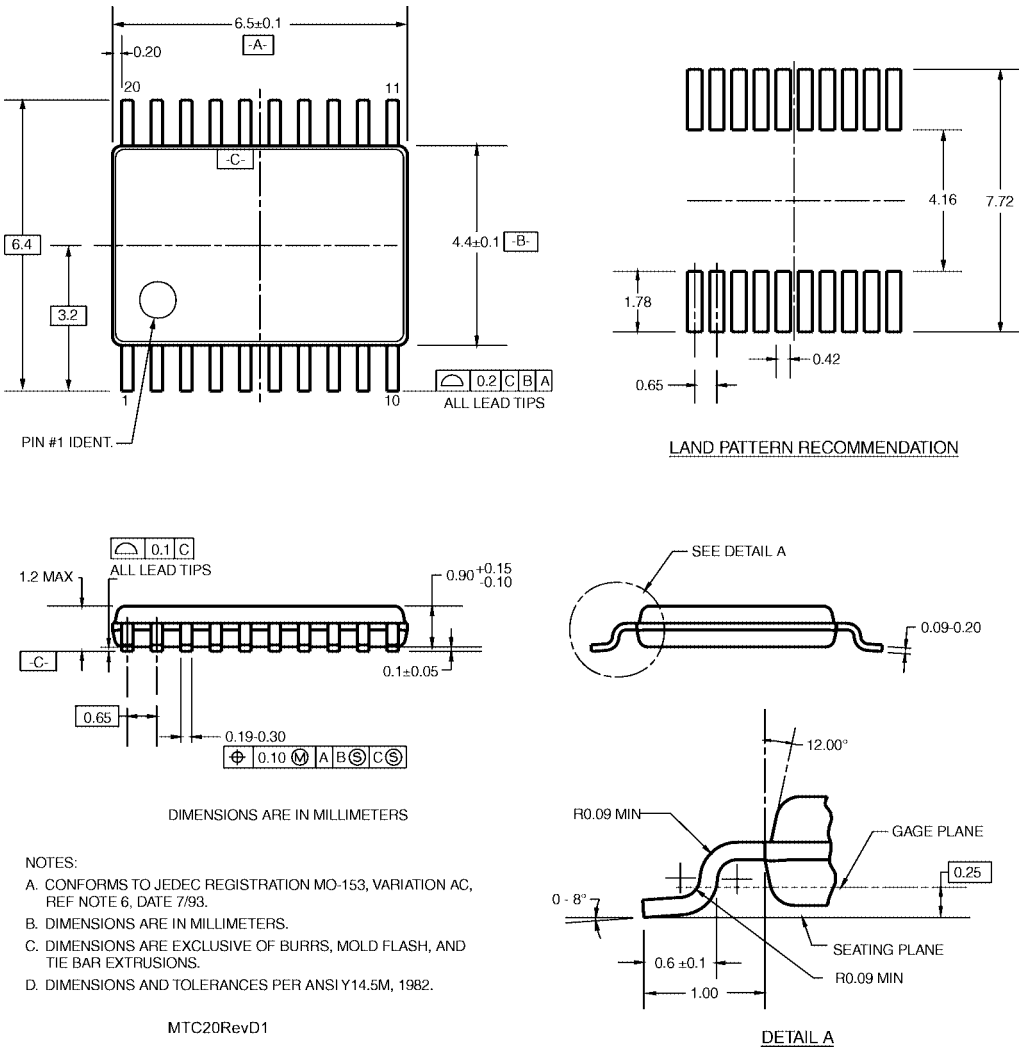
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

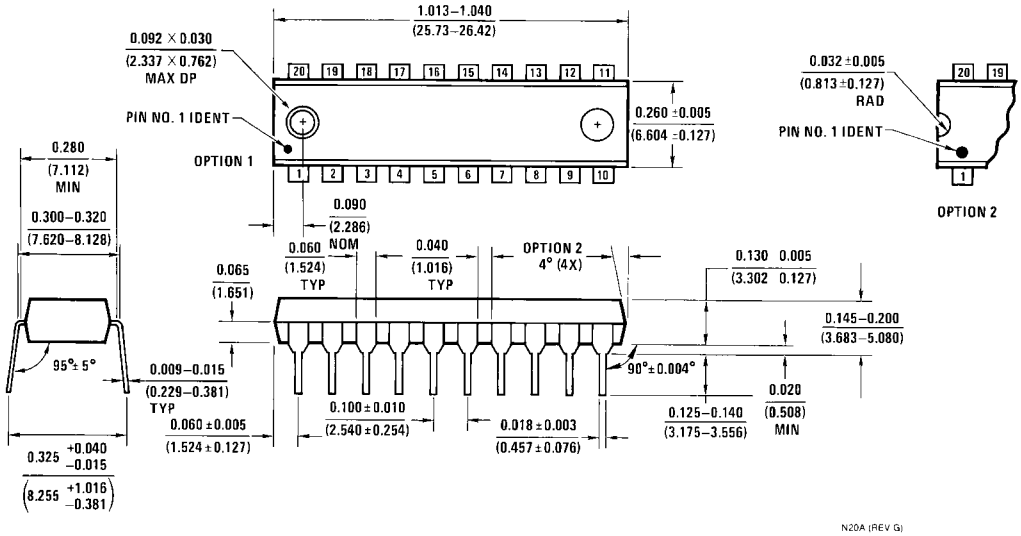
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised October 1999

74AC541 • 74ACT541
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The 74AC541 and 74ACT541 are octal buffer/line drivers designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

These devices are similar in function to the 74AC244 and 74ACTC244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes these devices especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

Features

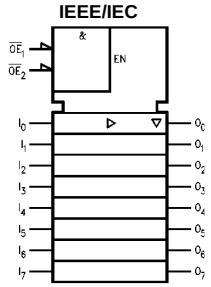
- I_{CC} and I_{OZ} reduced by 50%
- 3-STATE outputs
- Inputs and outputs opposite side of package, allowing easier interface to microprocessors
- Output source/sink 24 mA
- 74AC541 is a non-inverting option of the 74AC540
- 74ACT541 has TTL-compatible inputs

Ordering Code:

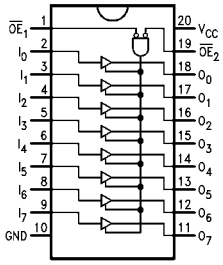
Order Number	Package Number	Package Description
74AC541SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC541PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT541SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT541PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level X = Immaterial L = LOW Voltage Level Z = High Impedance

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
AC: V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	
ACT: V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	2.0	5.5	8.0	1.5	9.0	ns
	Data to Output	5.0	1.5	4.0	6.0	1.0	6.5	
t_{PHL}	Propagation Delay	3.3	2.0	5.5	8.0	1.5	8.5	ns
	Data to Output	5.0	1.5	4.0	6.0	1.0	6.5	
t_{PZH}	Output Enable Time	3.3	3.0	8.0	11.5	3.0	12.5	ns
		5.0	2.0	6.0	8.5	1.5	9.5	
t_{PZL}	Output Enable Time	3.3	2.5	7.0	10.0	2.5	11.5	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t_{PHZ}	Output Disable Time	3.3	3.5	9.0	12.5	2.5	14.0	ns
		5.0	2.0	7.0	9.5	1.0	10.5	
t_{PLZ}	Output Disable Time	3.3	2.5	6.5	9.5	2.0	10.5	ns
		5.0	2.0	5.5	7.5	1.0	8.5	

Note 5: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	2.0	2.0		or $V_{CC} - 0.1V$
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	1.5	0.8	0.8		or $V_{CC} - 0.1V$
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9	V	$I_{OUT} = -50\ \mu A$
	Output Voltage	4.5	4.49	4.4	4.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH}
		5.5		4.86	4.76		$I_{OH} = -24$ mA
							$I_{OH} = -24$ mA (Note 6)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
	Output Voltage	4.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH}
		5.5		0.36	0.44		$I_{OH} = 24$ mA
							$I_{OH} = 24$ mA (Note 6)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 7)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 6: All outputs loaded; thresholds on input associated with output under test.

Note 7: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for ACT

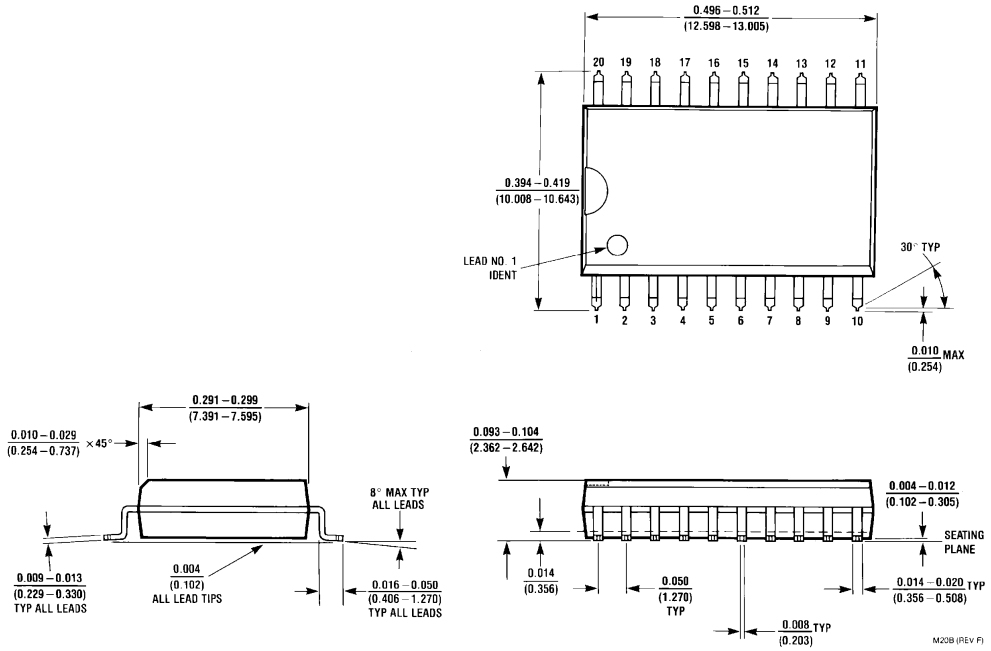
Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.0	4.5	7.0	2.0	7.5	ns
t_{PHL}	Data to Output		2.0	5.5	7.0	2.0	7.5	
t_{PZH}	Output Enable Time	5.0	2.0	5.0	9.0	2.0	9.5	ns
t_{PZL}			2.0	6.5	9.0	2.0	9.5	
t_{PHZ}	Output Disable Time	5.0	1.5	5.5	7.5	1.5	8.0	ns
t_{PLZ}			1.5	5.5	7.5	1.5	8.0	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

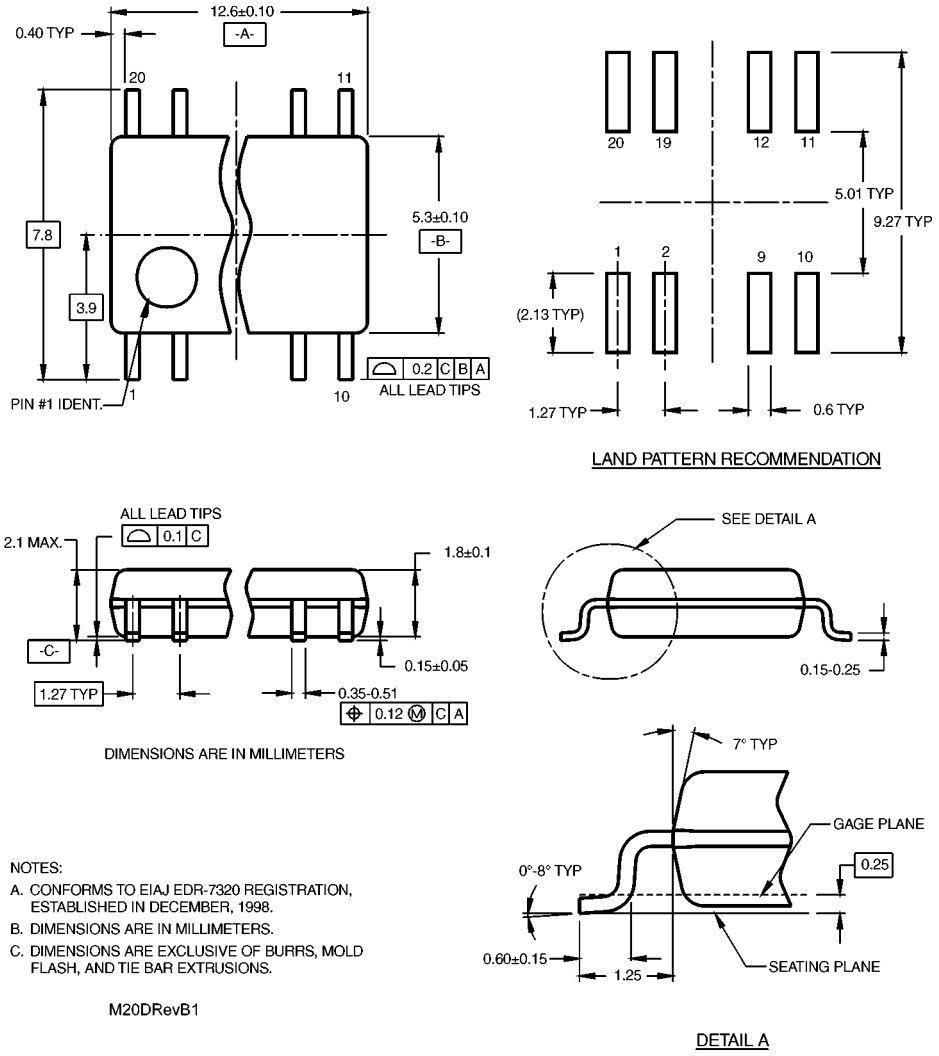
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance for AC	30.0	pF	V_{CC} = 5.0V
	Power Dissipation Capacitance for ACT	70.0		

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

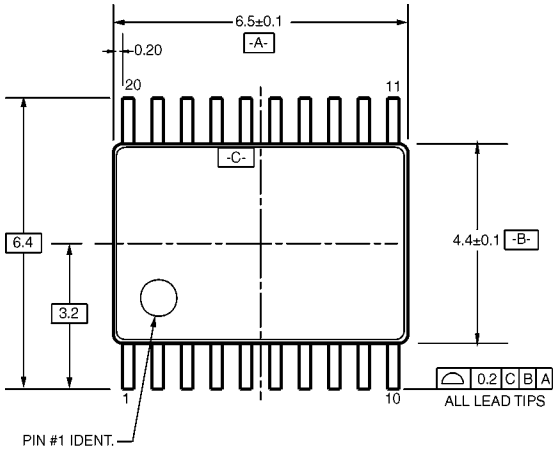
B. DIMENSIONS ARE IN MILLIMETERS.

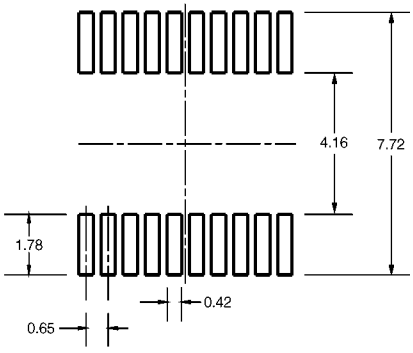
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

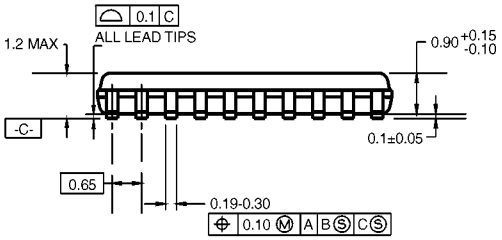
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

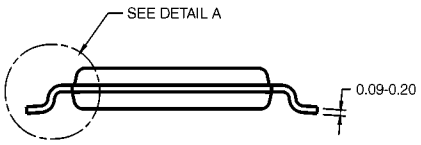
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

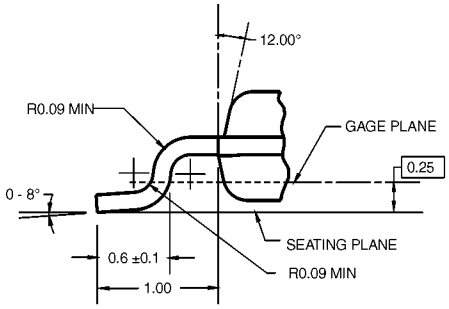
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

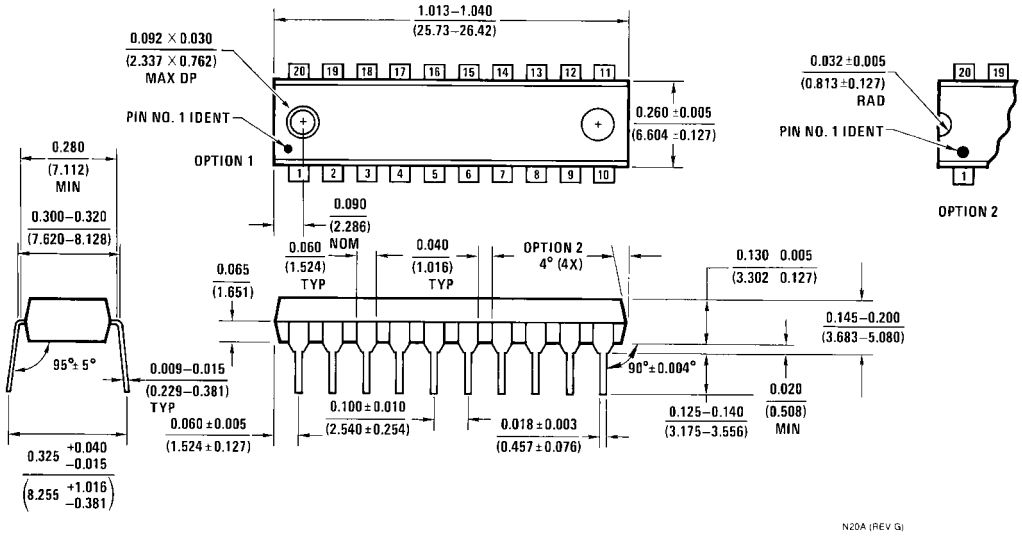
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised October 1999

74AC573 • 74ACT573
Octal Latch with 3-STATE Outputs

General Description

The 74AC573 and 74ACT573 are high-speed octal latches with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

The 74AC573 and 74ACT573 are functionally identical to the 74AC373 and 74ACT373 but with inputs and outputs on opposite sides.

Features

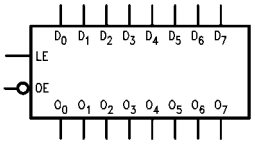
- I_{CC} and I_{OZ} reduced by 50%
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 74AC373 and 74ACT373
- 3-STATE outputs for bus interfacing
- Outputs source/sink 24 mA
- 74ACT573 has TTL-compatible inputs

Ordering Code:

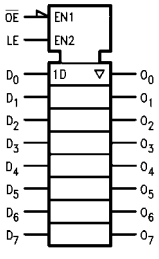
Order Number	Package Number	Package Description
74AC573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS--013, 0.300" Wide Body
74AC573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC573PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS--013, 0.300" Wide Body
74ACT573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT573PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

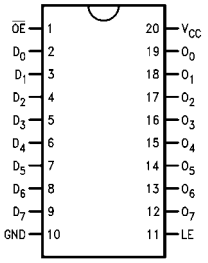
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Latch Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

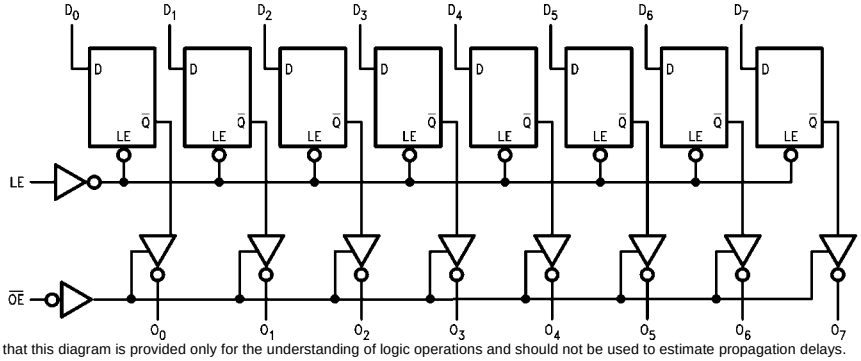
The 74AC573 and 74ACT573 contain eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW the latches store the information that was present on the D-type inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage
L = LOW Voltage
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J) (PDIP)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 3)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 3)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	0.5	8.5	10.5	2.5	11.0	ns
t_{PLH}	D_n to O_n	5.0	1.5	5.5	7.0	1.5	7.5	
t_{PLH}	Propagation Delay	3.3	2.5	8.5	12.0	2.5	12.5	ns
t_{PHL}	LE to O_n	5.0	2.0	6.0	8.0	2.0	8.5	
t_{PZL}	Output Enable Time	3.3	2.5	8.5	13.0	2.5	13.5	ns
t_{PZH}		5.0	1.5	6.0	8.5	1.5	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	9.0	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	6.0	9.5	1.0	10.0	

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V
Voltage Range 3.3 is 3.3V ± 0.3V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	0	3.0	3.0	ns
	D_n to LE	5.0	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	0	1.5	1.5	ns
	D_n to LE	5.0	0	1.5	1.5	
t_W	LE Pulse Width, HIGH	3.3	2.0	4.0	4.0	ns
		5.0	2.0	4.0	4.0	

Note 6: Voltage Range 5.0 is 5.0V ± 0.5V
Voltage Range 3.3 is 3.3V ± 0.3V

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
			5.5	1.5	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 7)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 7)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 8)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 7: All outputs loaded; thresholds on input associated with output under test.

Note 8: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay D_n to O_n	5.0	2.5	6.0	10.5	2.0	12.0	ns
t_{PLH}	Propagation Delay LE to O_n	5.0	3.0	6.0	10.5	2.5	12.0	ns
t_{PHL}	Propagation Delay LE to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PZH}	Output Enable Time	5.0	2.0	5.5	10.0	1.5	11.0	ns
t_{PZL}	Output Enable Time	5.0	1.5	5.5	9.5	1.5	10.5	ns
t_{PHZ}	Output Disable Time	5.0	2.5	6.5	11.0	1.5	12.5	ns
t_{PLZ}	Output Disable Time	5.0	1.5	5.0	8.5	1.0	9.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

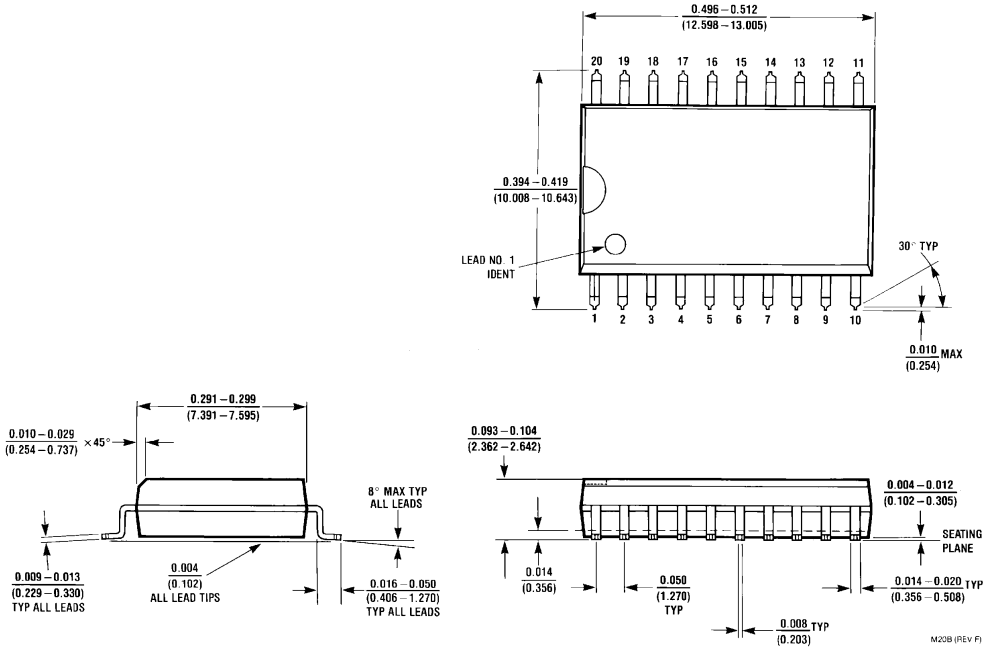
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	1.5	3.0	3.5	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	–1.5	0	0	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	3.5	4.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

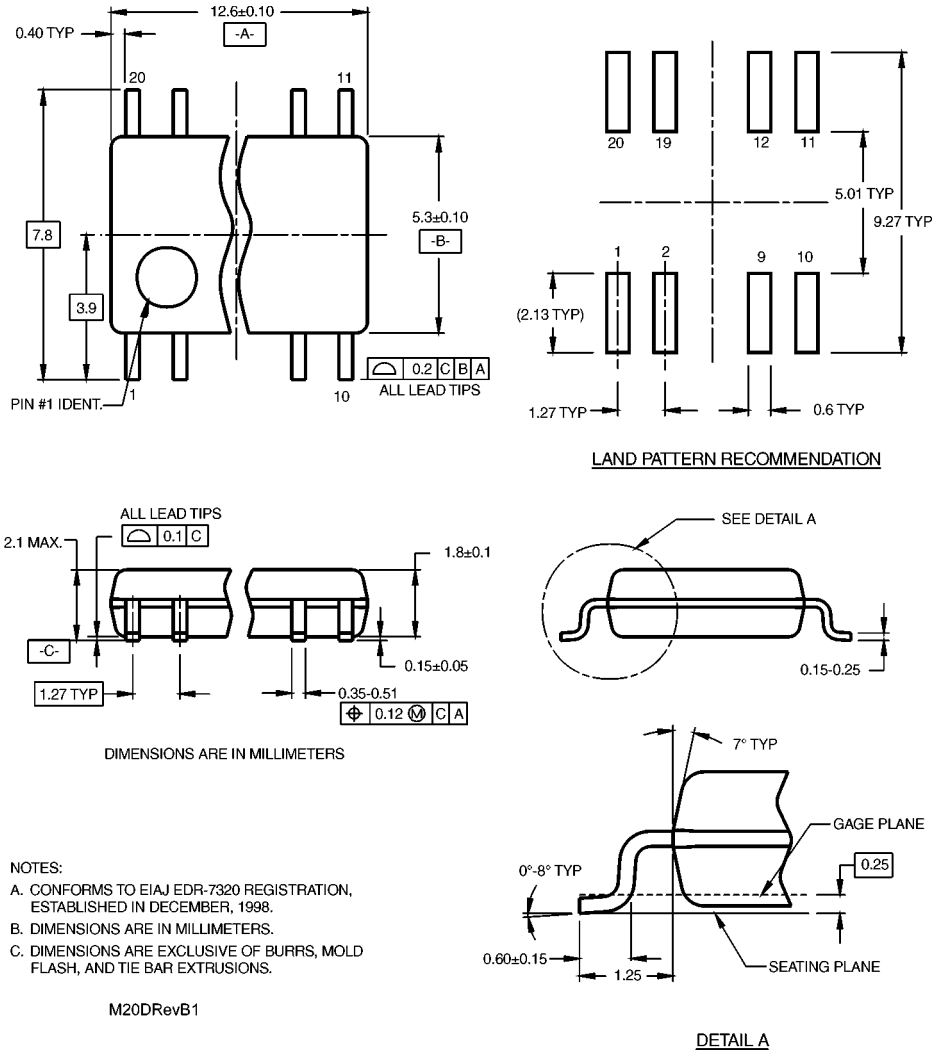
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	5.0	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance for AC for ACT	25.0 42.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

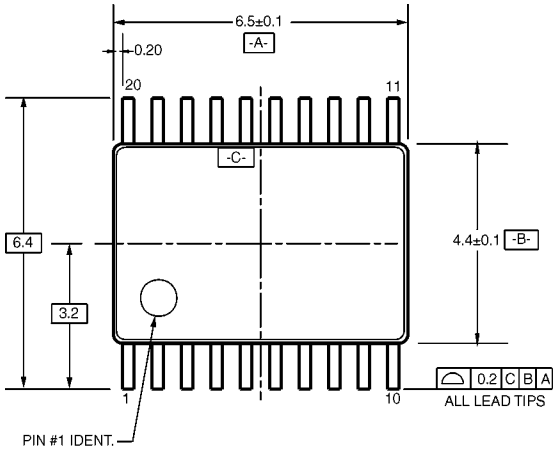
B. DIMENSIONS ARE IN MILLIMETERS.

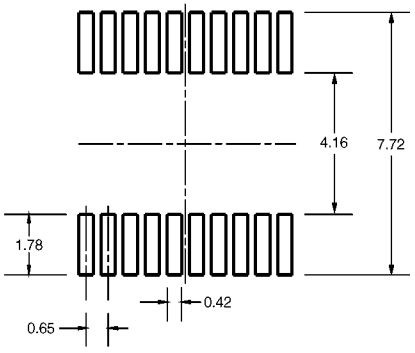
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

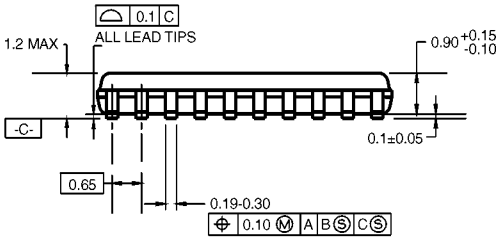
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

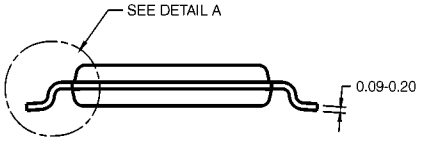
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

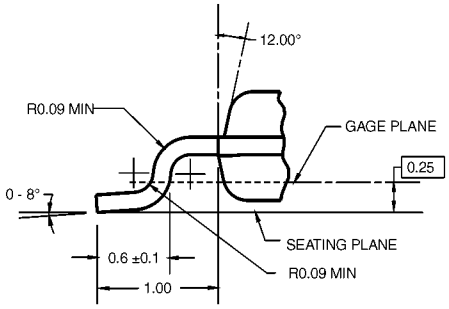
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

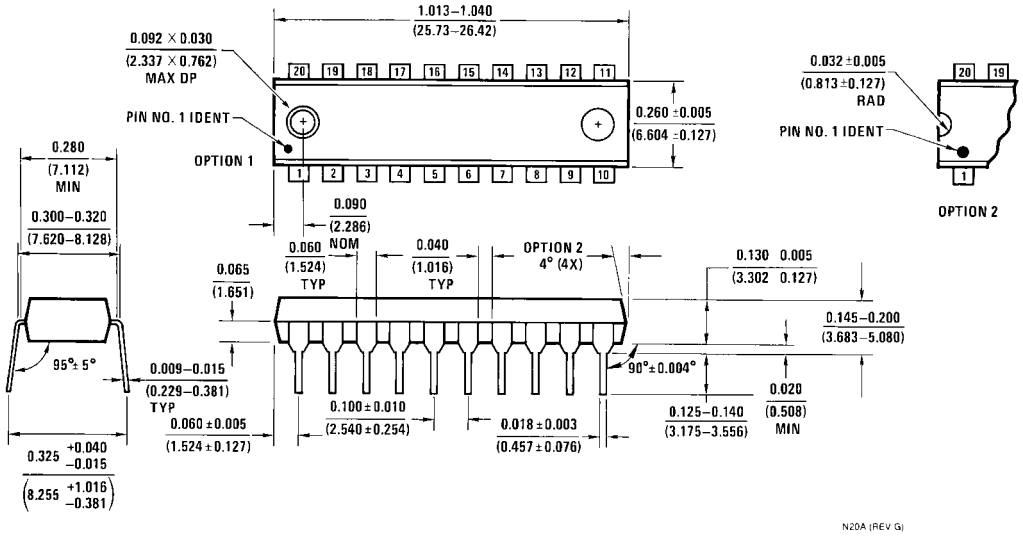
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

September 1988
Revised November 1999

74AC574 • 74ACT574
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The AC/ACT574 is a high-speed, low power octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable ($\overline{OE}$). The information presented to the D-type inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The AC/ACT574 is functionally identical to the AC/ACT374 except for the pinouts.

Features

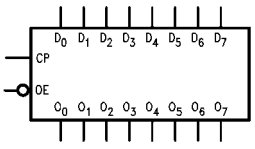
- I_{CC} and I_{OZ} reduced by 50%
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to AC/ACT374
- 3-STATE outputs for bus-oriented applications
- Outputs source/sink 24 mA
- ACT574 has TTL-compatible inputs

Ordering Code:

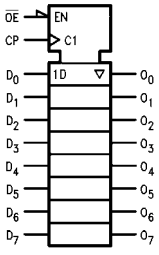
Order Number	Package Number	Package Description
74AC574SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC574PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT574SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-01
74ACT574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT574PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

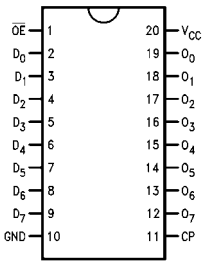
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

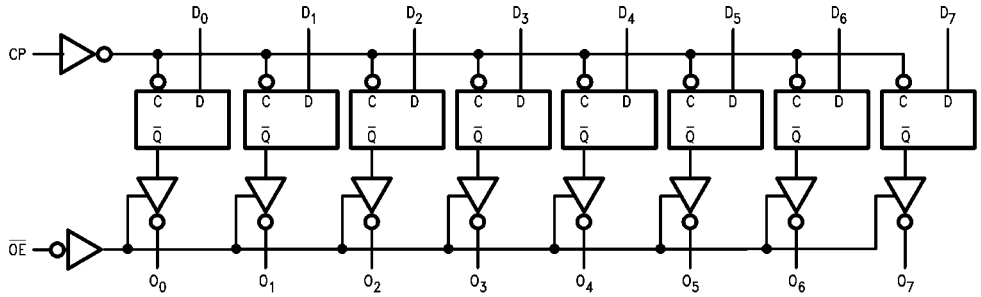
The AC/ACT574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O_N	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	↗	L	L	Z	Load
H	↗	H	H	Z	Load
L	↗	L	L	L	Data Available
L	↗	H	H	H	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
↗ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		3.0		2.56	2.46		V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −12 mA
		5.5		4.86	4.76		I_{OH} = −24 mA I_{OH}
							I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL}or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum						V_I (OE) = V_{IL}, V_{IH}
	3-STATE	5.5		±0.25	±2.5	μA	V_I = V_{CC}, V_{GND}
	Leakage Current						V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	µA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	3.3	75	112		60		MHz
		5.0	95	153		85		
t_{PLH}	Propagation Delay CP to O_n	3.3	3.5	8.5	13.5	3.5	15.0	ns
		5.0	2.0	6.0	9.5	2.0	11.0	
t_{PHL}	Propagation Delay CP to O_n	3.3	3.5	7.5	12.0	3.5	13.5	ns
		5.0	2.0	5.5	8.5	2.0	9.5	
t_{PZH}	Output Enable Time	3.3	2.5	7.0	11.0	2.5	12.0	ns
		5.0	2.0	5.0	8.5	2.0	9.0	
t_{PZL}	Output Enable Time	3.3	3.0	6.5	10.5	3.0	11.5	ns
		5.0	2.0	5.0	8.0	1.5	9.0	
t_{PHZ}	Output Disable Time	3.3	3.5	7.5	12.0	2.5	13.0	ns
		5.0	2.0	6.0	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	3.3	2.0	5.5	9.0	1.5	10.0	ns
		5.0	1.0	4.5	7.5	1.0	8.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Set-Up Time, HIGH or LOW	3.3	0.5	2.5	3.0	ns
	D_n to CP	5.0	0	1.5	2.0	
t_H	Hold Time, HIGH or LOW	3.3	−0.5	1.5	1.5	ns
	D_n to CP	5.0	0	1.5	1.5	
t_W	CP Pulse Width	3.3	3.5	6.0	7.0	ns
	HIGH or LOW	5.0	2.0	4.0	5.0	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	100	110		85		ns
t_{PLH}	Propagation Delay CP to O_n	5.0	2.5	7.0	11.0	2.0	12.0	ns
t_{PHL}	Propagation Delay CP to O_n	5.0	2.0	6.5	10.0	1.5	11.0	ns
t_{PZH}	Output Enable Time	5.0	2.0	6.4	9.5	1.5	10.0	ns
t_{PZL}	Output Enable Time	5.0	2.0	6.0	9.0	1.5	10.0	ns
t_{PHZ}	Output Disable Time	5.0	2.0	7.0	10.5	1.5	11.5	ns
t_{PLZ}	Output Disable Time	5.0	2.0	5.5	8.5	1.5	9.0	ns

Note 9: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements for ACT

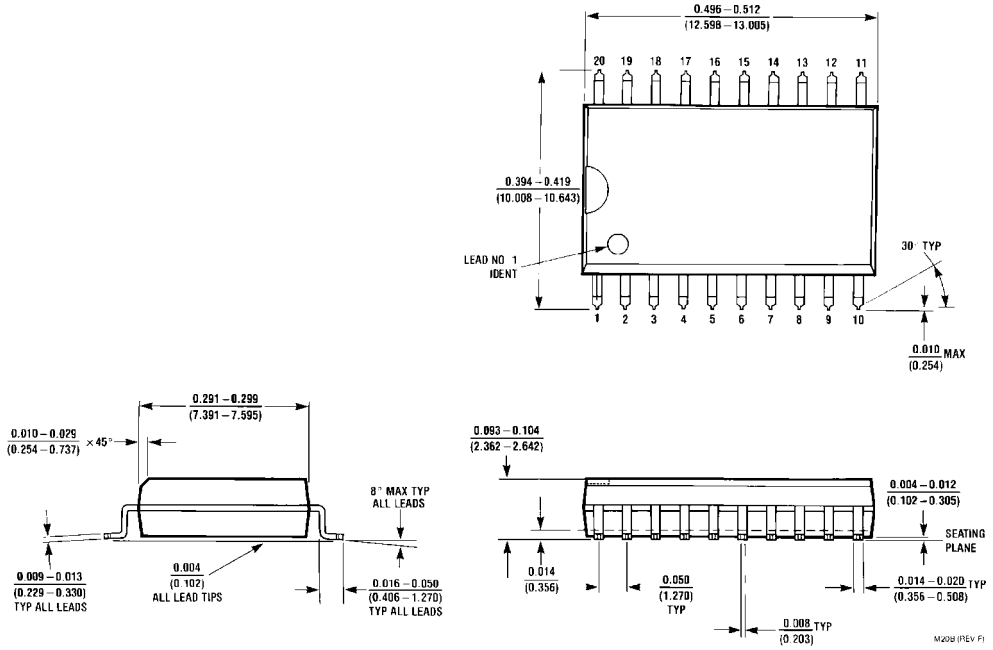
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum	
t_S	Set-Up Time, HIGH or LOW D_n to CP	5.0	1.5	2.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	−0.5	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.5	4.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

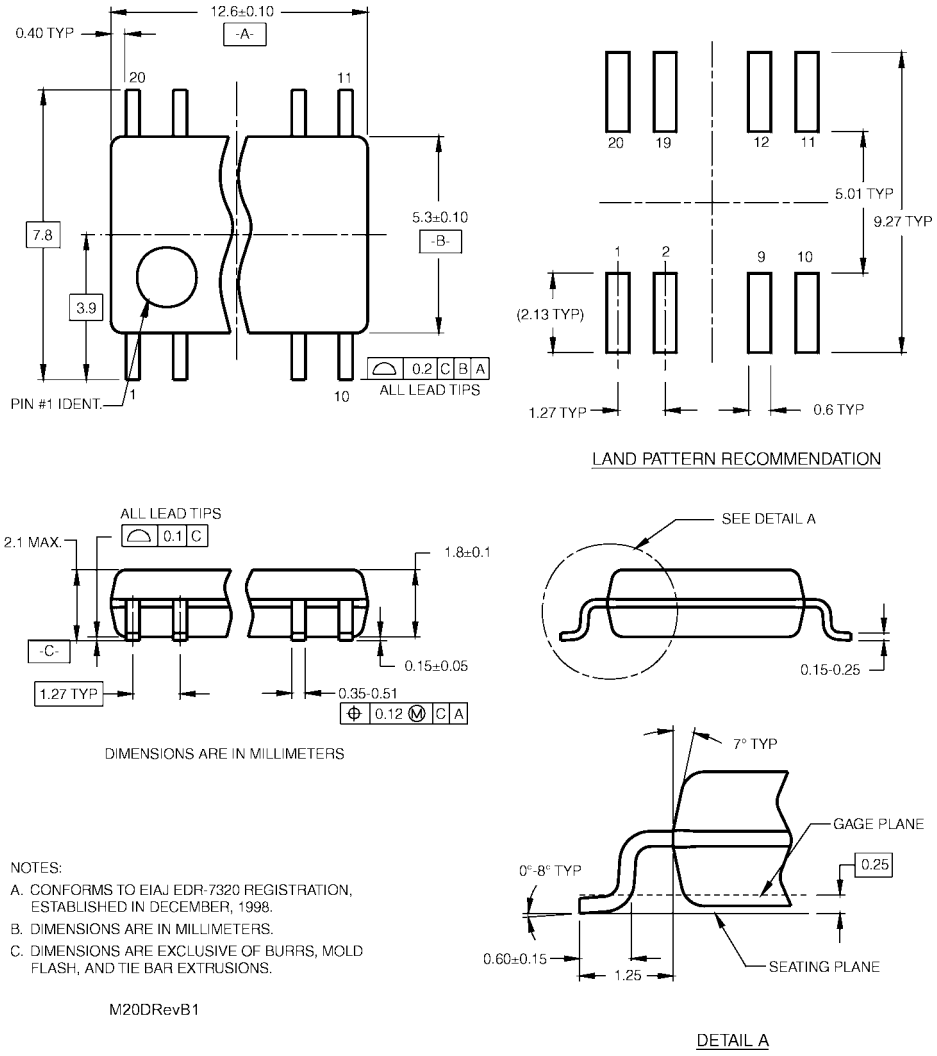
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

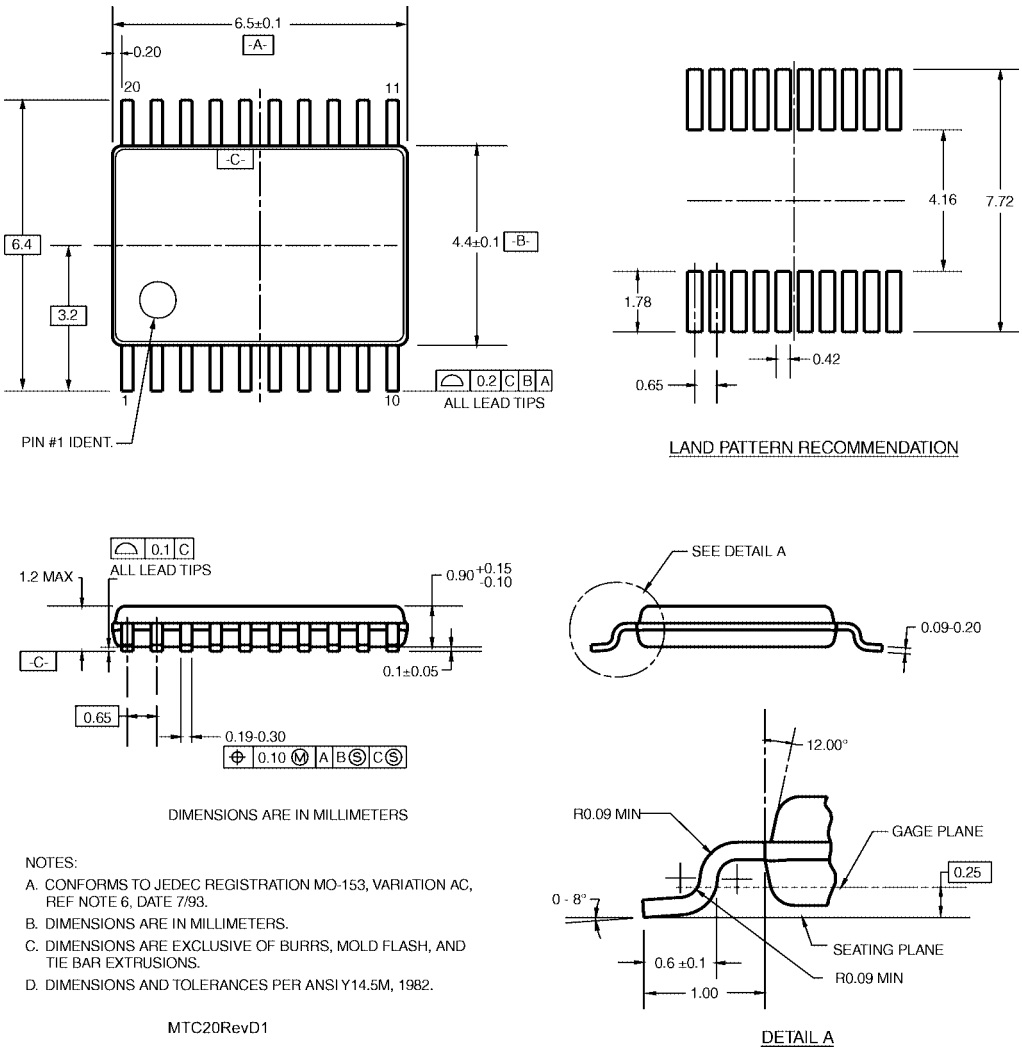
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ Type II 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

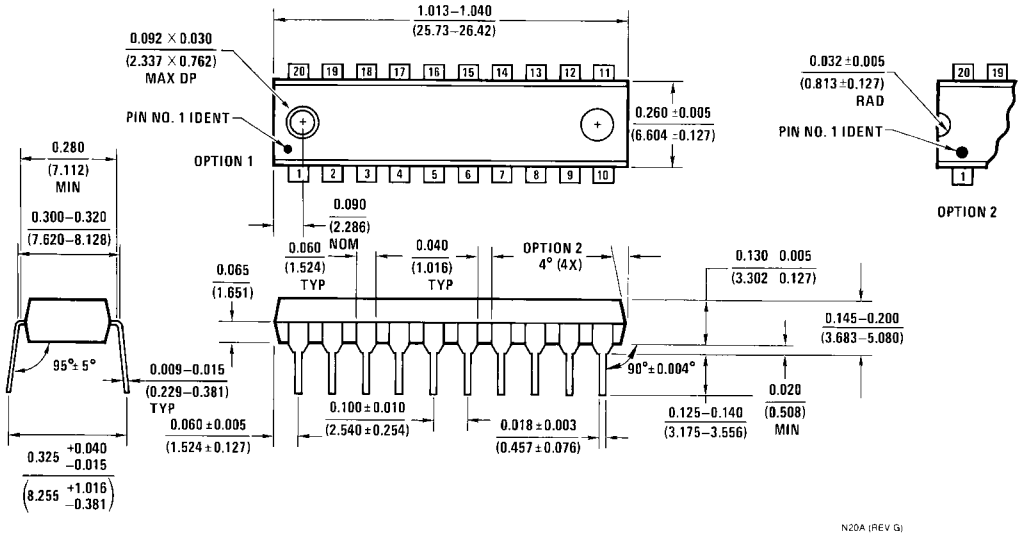
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised December 1998

74AC646 • 74ACT646
Octal Transceiver/Register with 3-STATE Outputs

General Description

The AC/ACT646 consist of registered bus transceiver circuits, with outputs, D-type flip-flops and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate clock pin (CPAB or CPBA). The four fundamental data handling functions available are illustrated in Figure 1, Figure 2, Figure 3, and Figure 4.

Features

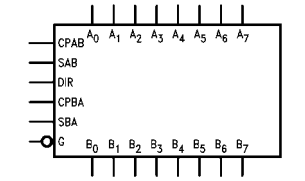
- Independent registers for A and B buses
- Multiplexed real-time and stored data transfers
- 3-STATE outputs
- 300 mil dual-in-line package
- Outputs source/sink 24 mA
- ACT646 has TTL compatible inputs

Ordering Code:

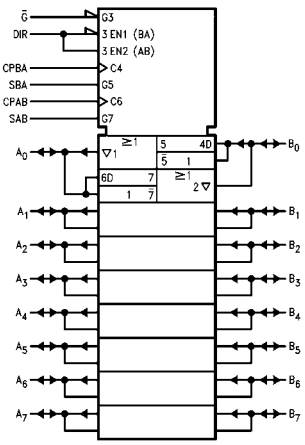
Order Number	Package Number	Package Description
74AC646SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC646SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
74ACT646SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols

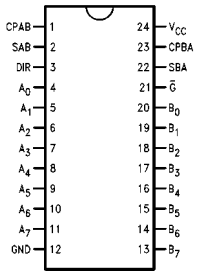


IEEE/IEC



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
A_0–A_7	Data Register A Inputs
	Data Register A Outputs
B_0–B_7	Data Register B Inputs
	Data Register B Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
$\overline{G}$	Output Enable Input
DIR	Direction Control Input

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Function Table

Inputs						Data I/O (Note 1)		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n —Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

Real Time Transfer A-Bus to B-Bus

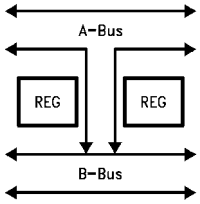


FIGURE 1.

Real Time Transfer B-Bus to A-Bus

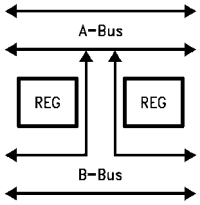


FIGURE 2.

Storage from Bus to Register

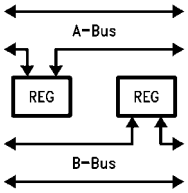


FIGURE 3.

Transfer from Register to Bus

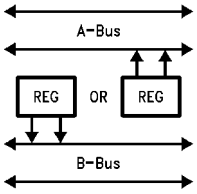
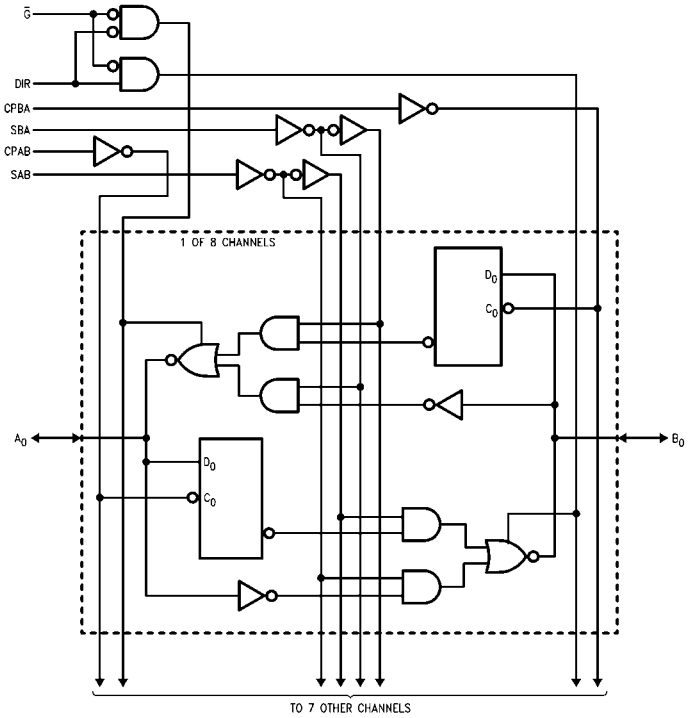


FIGURE 4.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		I_{OUT} = −50 μA
	Output Voltage	4.5	4.49	4.4	4.4	V	
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		I_{OUT} = 50 μA
	Output Voltage	4.5	0.001	0.1	0.1	V	
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OH} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OH} = 24 mA (Note 3)
I_{IN} (Note 5)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 5)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.6	±6.0	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 6)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 6)
	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	$V_I = V_{CC}$, GND
	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 7)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	$V_{IN} = V_{CC}$ or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.6	±6.0	µA	V_I (OE) = V_{IL}, V_{IH} $V_I = V_{CC}$, GND $V_O = V_{CC}$, GND

Note 6: All outputs loaded; thresholds on input associated with output under test.

Note 7: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
t_{PLH}	Propagation Delay Clock to Bus	3.3	4.0	10.5	16.5	3.0	18.5	ns
		5.0	2.5	7.5	12.0	2.0	13.0	
t_{PHL}	Propagation Delay Clock to Bus	3.3	3.0	9.5	14.5	2.5	16.0	ns
		5.0	2.0	6.5	10.5	1.5	11.5	
t_{PLH}	Propagation Delay Bus to Bus	3.3	2.5	7.5	12.0	2.0	13.5	ns
		5.0	1.5	5.0	8.0	1.0	9.0	
t_{PHL}	Propagation Delay Bus to Bus	3.3	1.5	7.5	12.5	1.5	13.5	ns
		5.0	1.5	5.0	9.0	1.0	9.5	
t_{PLH}	Propagation Delay SBA or SAB to A_n or B_n (w/ A_n or B_n HIGH or LOW)	3.3	2.0	8.5	13.5	1.5	15.5	
		5.0	1.5	6.0	10.0	1.5	11.0	ns
t_{PHL}	Propagation Delay SBA or SAB to A_n or B_n (w/ A_n or B_n HIGH or LOW)	3.3	1.5	8.5	13.5	1.5	15.0	
		5.0	1.5	6.0	10.0	1.5	11.0	ns
t_{PZH}	Enable Time $\overline{G}$ to A_n or B_n	3.3	2.5	7.0	11.5	2.0	12.5	ns
		5.0	1.5	5.0	8.5	1.5	9.0	

AC Electrical Characteristics for AC (Continued)

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PZL}	Enable Time	3.3	2.5	7.5	12.5	2.0	14.0	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	5.5	9.0	1.5	10.0	
t_{PHZ}	Disable Time	3.3	3.0	8.0	12.5	2.5	13.5	ns
	$\overline{G}$ to A_n or B_n	5.0	2.0	6.5	10.0	2.0	11.0	
t_{PLZ}	Disable Time	3.3	2.0	7.5	12.0	2.0	13.5	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	6.0	9.5	1.5	10.5	
t_{PZH}	Enable Time	3.3	2.0	6.5	11.0	1.5	12.0	ns
	DIR to A_n or B_n	5.0	1.5	5.0	7.5	1.0	8.5	
t_{PZL}	Enable Time	3.3	2.5	7.0	11.5	2.0	13.0	ns
	DIR to A_n or B_n	5.0	1.5	5.0	8.0	1.0	9.0	
t_{PHZ}	Disable Time	3.3	2.5	7.5	11.5	1.5	12.5	ns
	DIR to A_n or B_n	5.0	1.5	5.5	9.5	1.5	10.0	
t_{PLZ}	Disable Time	3.3	1.5	7.5	12.0	1.5	13.5	ns
	DIR to A_n or B_n	5.0	1.5	5.5	9.5	1.5	10.5	

Note 8: Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	2.0	5.0	5.5	ns
	Bus to Clock	5.0	1.5	4.0	4.5	
t_H	Hold Time, HIGH or LOW	3.3	−1.5	0	0	ns
	Bus to Clock	5.0	−0.5	0.5	1.0	
t_W	Clock Pulse Width	3.3	2.0	3.5	4.5	ns
	HIGH or LOW	5.0	2.0	3.5	3.5	

Note 9: Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Clock to Bus	5.0	3.5	12.0	14.5	3.0	16.0	ns
t_{PHL}	Propagation Delay Clock to Bus	5.0	4.0	12.0	14.5	3.5	16.0	ns
t_{PLH}	Propagation Delay Bus to Bus	5.0	3.0	8.5	10.5	2.5	11.5	ns
t_{PHL}	Propagation Delay Bus to Bus	5.0	2.5	8.5	10.5	2.0	11.5	ns
t_{PLH}	Propagation Delay SBA or SAB to A_n to B_n (w/A_n or B_n HIGH or LOW)	5.0	3.0	9.5	11.5	2.5	12.5	ns
t_{PHL}	Propagation Delay SBA or SAB to A_n to B_n (w/A_n or B_n HIGH or LOW)	5.0	3.0	9.5	11.5	2.5	12.5	ns
t_{PZH}	Enable Time $\overline{G}$ to A_n or B_n	5.0	2.0	9.0	11.0	1.5	12.0	ns
t_{PZL}	Enable Time $\overline{G}$ to A_n or B_n	5.0	3.5	9.0	11.0	3.0	12.0	ns
t_{PHZ}	Disable Time $\overline{G}$ to A_n or B_n	5.0	5.0	10.5	13.0	4.5	14.5	ns
t_{PLZ}	Disable Time $\overline{G}$ to A_n or B_n	5.0	3.5	10.0	12.5	3.0	14.0	ns
t_{PZH}	Enable Time DIR to A_n or B_n	5.0	2.0	6.5	10.5	1.5	11.5	ns
t_{PZL}	Enable Time DIR to A_n or B_n	5.0	3.5	6.5	10.5	3.0	11.5	ns
t_{PHZ}	Disable Time DIR to A_n or B_n	5.0	5.0	8.5	12.5	4.5	13.5	ns
t_{PLZ}	Disable Time DIR to A_n or B_n	5.0	3.5	8.5	12.5	3.0	13.5	ns

Note 10: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements for ACT

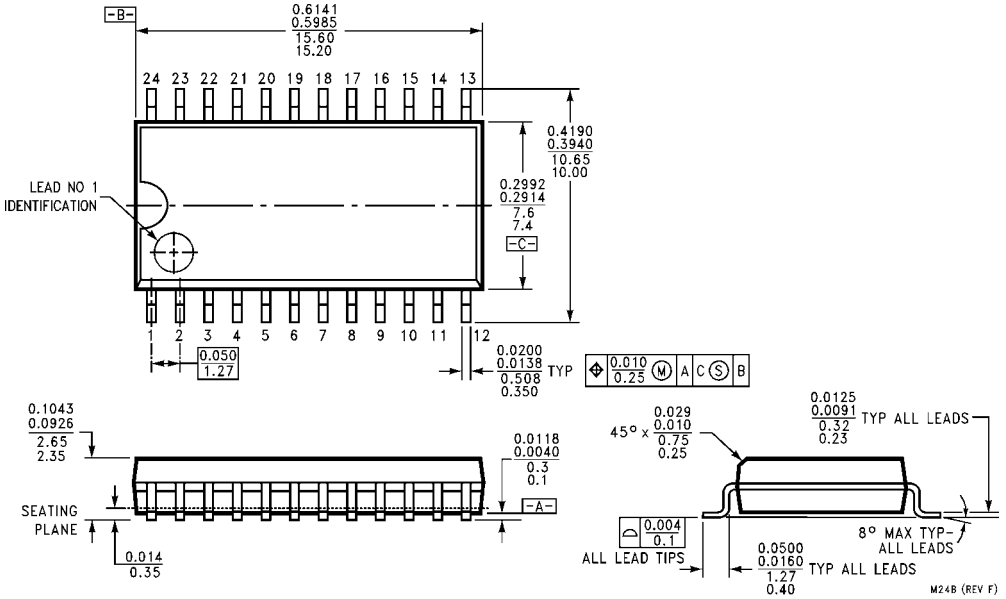
Symbol	Parameter	V_{CC} (V) (Note 11)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW BUS to Clock	5.0	2.5	7.0	8.0	ns
t_H	Hold Time, HIGH or LOW Bus to Clock	5.0	0	2.5	2.5	ns
t_W	Clock Pulse Width HIGH or LOW	5.0	4.5	7.0	8.0	ns

Note 11: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

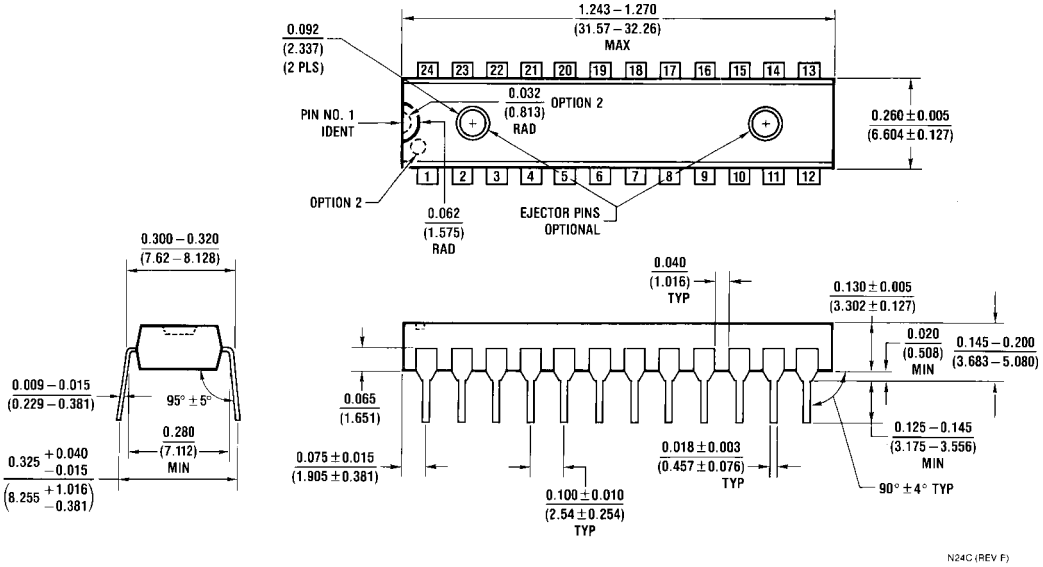
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
$C_{I/O}$	Input/Output Capacitance	15.0	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	60.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1988
Revised December 1998

74AC648
Octal Transceiver/Register with 3-STATE Outputs

General Description

The AC648 consists of registered bus transceiver circuits, with outputs, D-type flip-flops and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate clock pin (CPAB or CPBA). The four fundamental data handling functions available are illustrated in Figure 1, Figure 2, Figure 3, and Figure 4.

Features

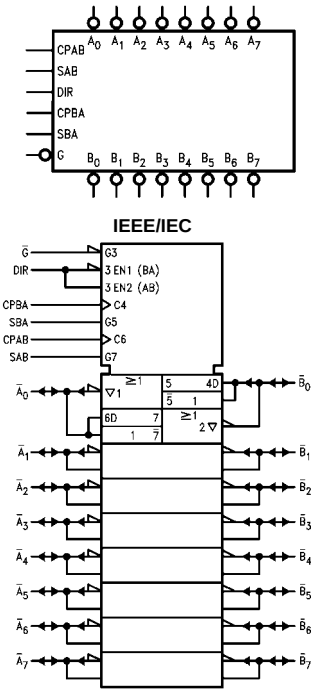
- Independent registers for A and B buses
- Multiplexed real-time and stored data transfers
- 3-STATE outputs
- 300 mil slim dual-in-line package
- Outputs source/sink 24 mA
- Inverted data to output

Ordering Code:

Order Number	Package Number	Package Description
74AC648SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74AC648SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

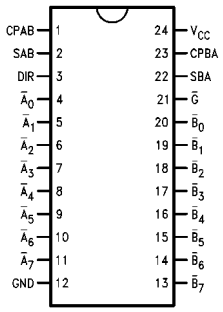
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
$\overline{A}_0$–$\overline{A}_7$	Data Register A Inputs, Data Register A 3-STATE Outputs
$\overline{B}_0$– $\overline{B}_7$	Data Register B Inputs, Data Register B 3-STATE Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
DIR, $\overline{G}$	Output Enable Inputs

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Function Table

Inputs						Data I/O (Note 1)		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n —Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Irrelevant
↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the clock inputs.

Real Time Transfer
A-Bus to B-Bus

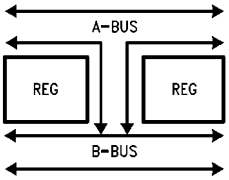


FIGURE 1.

Real Time Transfer
B-Bus to A-Bus

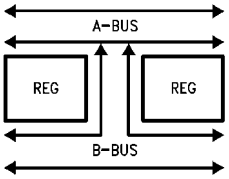


FIGURE 2.

Storage from
Bus to Register

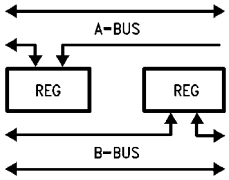


FIGURE 3.

Transfer from
Register to Bus

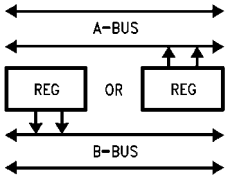
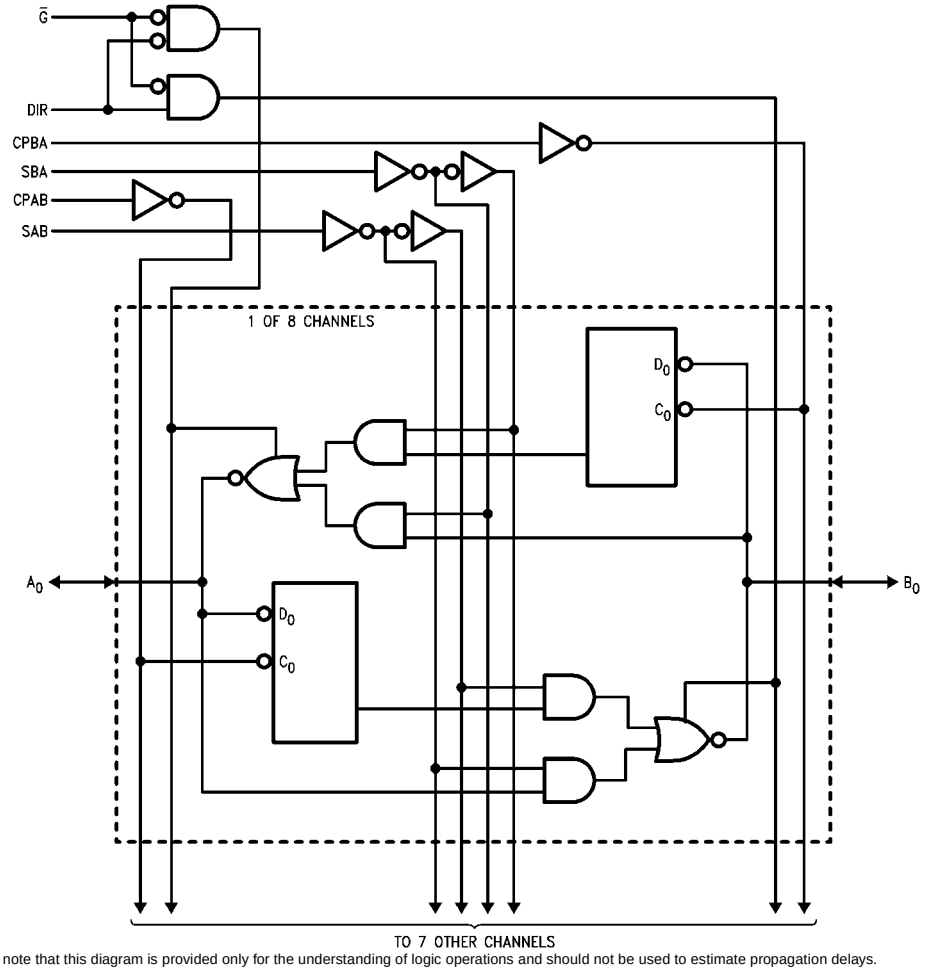


FIGURE 4.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH}= −12 mA
		4.5		3.86	3.76	V	I_{OH}= −24 mA
		5.5		4.86	4.76		I_{OH}= −24 mA (Note 3)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL}= 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{IN} (Note 5)	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 5)	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.6	±6.0	µA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	10.0	15.5	1.5	17.0	ns
	Clock to Bus	5.0	1.5	7.0	11.0	1.5	12.0	
t_{PHL}	Propagation Delay	3.3	1.5	8.5	13.5	1.5	14.5	ns
	Clock to Bus	5.0	1.5	6.0	10.5	1.5	11.5	
t_{PLH}	Propagation Delay	3.3	1.5	6.0	10.0	1.5	11.0	ns
	Bus to Bus	5.0	1.5	4.0	7.0	1.0	7.5	
t_{PHL}	Propagation Delay	3.3	1.5	5.5	9.0	1.5	10.0	ns
	Bus to Bus	5.0	1.5	3.5	7.5	1.0	8.0	
t_{PLH}	Propagation Delay	3.3	1.5	7.5	12.5	1.5	14.0	
	SBA or SAB to A_n or B_n	5.0	1.5	5.5	9.0	1.5	10.0	ns
	(with A_n or B_n HIGH or LOW)							
t_{PHL}	Propagation Delay	3.3	1.5	7.5	12.5	1.5	14.0	
	SBA or SAB to A_n or B_n	5.0	1.5	5.5	9.5	1.5	10.5	ns
	(with A_n or B_n HIGH or LOW)							
t_{PZH}	Enable Time	3.3	1.5	6.5	11.0	1.0	11.5	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	5.0	8.0	1.0	9.0	
t_{PZL}	Enable Time	3.3	1.5	7.0	11.0	1.0	12.5	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	5.0	8.0	1.0	9.0	
t_{PHZ}	Disable Time	3.3	1.5	7.5	12.0	1.0	13.0	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	6.0	10.0	1.0	11.0	
t_{PLZ}	Disable Time	3.3	1.5	7.0	11.5	1.0	12.5	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	5.5	9.0	1.0	10.0	
t_{PZH}	Enable Time	3.3	1.5	6.0	12.5	1.0	14.0	ns
	DIR to A_n or B_n	5.0	1.5	4.5	9.5	1.0	10.5	
t_{PZL}	Enable Time	3.3	1.5	6.5	13.0	1.5	14.5	ns
	DIR to A_n or B_n	5.0	1.5	4.5	9.0	1.0	10.5	
t_{PHZ}	Disable Time	3.3	1.5	7.0	11.5	1.0	13.5	ns
	DIR to A_n or B_n	5.0	1.5	5.5	9.0	1.0	10.0	
t_{PLZ}	Disable Time	3.3	1.5	7.0	13.5	1.5	15.0	ns
	DIR to A_n or B_n	5.0	1.5	5.0	9.5	1.0	10.0	

Note 6: Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

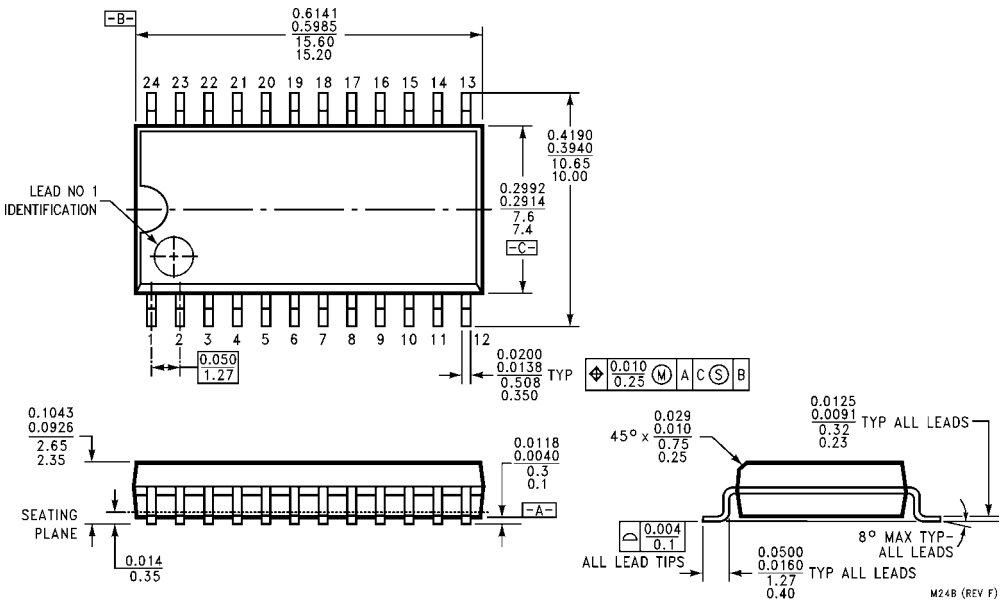
Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW,	3.3	2.0	3.0	3.5	ns
	Bus to Clock	5.0	1.5	2.0	2.0	
t_H	Hold Time, HIGH or LOW,	3.3	−1.5	0	0	ns
	Bus to Clock	5.0	−0.5	1.0	1.0	
t_W	Clock Pulse Width	3.3	2.0	3.5	4.0	ns
	HIGH or LOW	5.0	2.0	3.0	3.0	

Note 7: Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

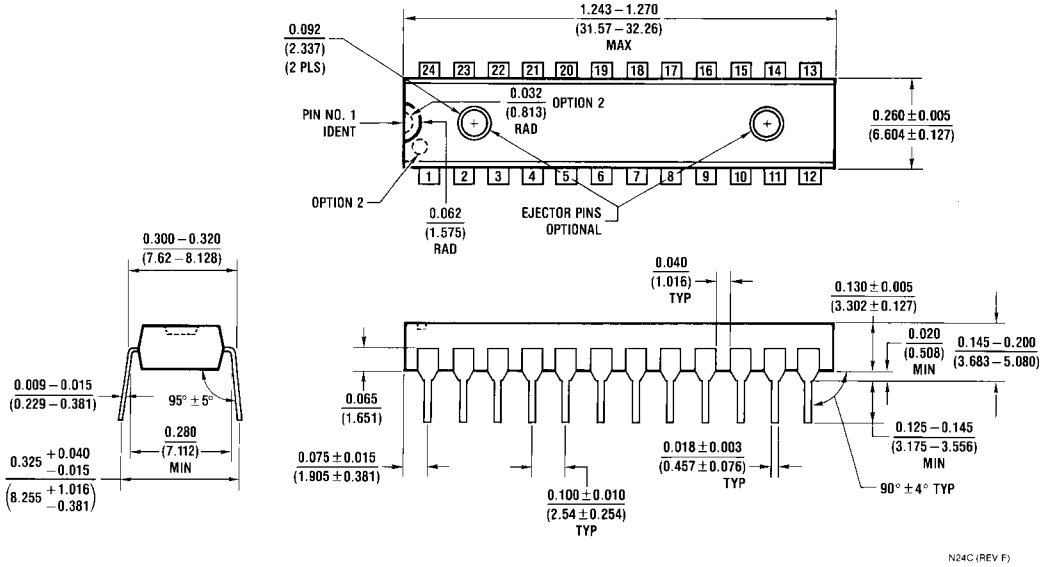
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	65.0	pF	V_{CC} = 5.0V
$C_{I/O}$	Input/Output Capacitance	15.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74AC74 • 74ACT74
Dual D-Type Positive Edge-Triggered Flip-Flop

General Description

The AC/ACT74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. Clock triggering occurs at a voltage level of the clock pulse and is not directly related to the transition time of the positive-going pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

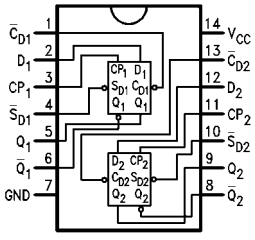
- I_{CC} reduced by 50%
- Output source/sink 24 mA
- ACT74 has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74AC74SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC74MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC74PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT74SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACT74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT74MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT74PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

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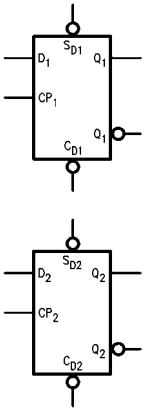
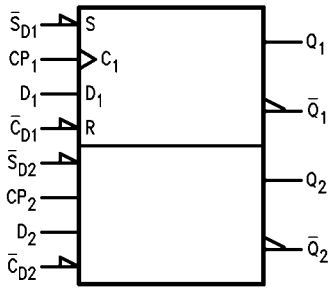
Logic Symbols



IEEE/IEC



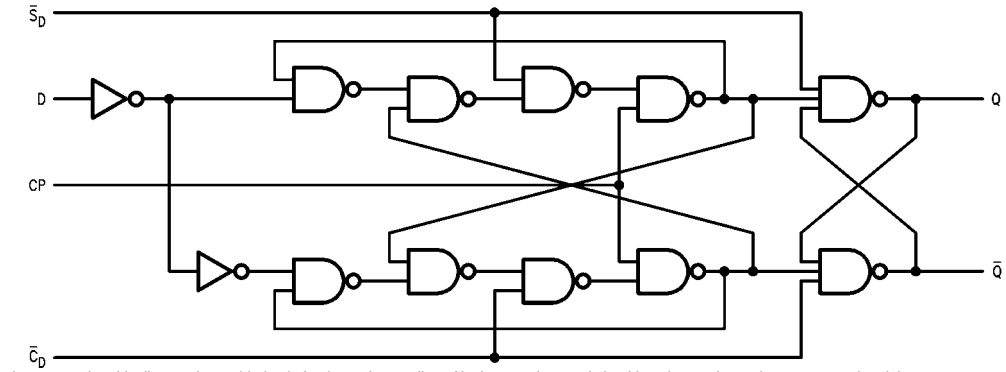
Truth Table

(Each Half)

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	⌐	H	H	L
H	H	⌐	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
Q_0 ($\overline{Q}_0$) = Previous Q ($\overline{Q}$) before LOW-to-HIGH Transition of Clock

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Level Input	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
	Voltage	5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Level Input	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
	Voltage	5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH	3.0	2.99	2.9	2.9		
	Level Output	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 m
		5.5		4.86	4.76		I_{OH} = −24 m (Note 2)
V_{OL}	Maximum LOW	3.0	0.002	0.1	0.1		
	Level Output	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum InputLeakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Output Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 5)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 6)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	3.3	100	125		95		MHz
		5.0	140	160		125		
t_{PLH}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.3	3.5	8.0	12.0	2.5	13.0	ns
		5.0	2.5	6.0	9.0	2.0	10.0	
t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.3	4.0	10.5	12.0	3.5	13.5	ns
		5.0	3.0	8.0	9.5	2.5	10.5	
t_{PLH}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	3.3	4.5	8.0	13.5	4.0	16.0	ns
		5.0	3.5	6.0	10.0	3.0	10.5	
t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	3.3	3.5	8.0	14.0	3.5	14.5	ns
		5.0	2.5	6.0	10.0	2.5	10.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Set-up Time, HIGH or LOW	3.3	1.5	4.0	4.5	ns
	D_n to CP_n	5.0	1.0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	–2.0	0.5	0.5	ns
	D_n to CP_n	5.0	–1.5	0.5	0.5	
t_W	CP_n or $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$	3.3	3.0	5.5	7.0	ns
	Pulse Width	5.0	2.5	4.5	5.0	
t_{rec}	Recovery Time	3.3	–2.5	0	0	ns
	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP	5.0	–2.0	0	0	

Note 8: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	145	210		125		MHz
t_{PLH}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	5.0	3.0	5.5	9.5	2.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	5.0	3.0	6.0	10.0	3.0	11.5	ns
t_{PLH}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	5.0	4.0	7.5	11.0	4.0	13.0.	ns
t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	5.0	3.5	6.0	10.0	3.0	11.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

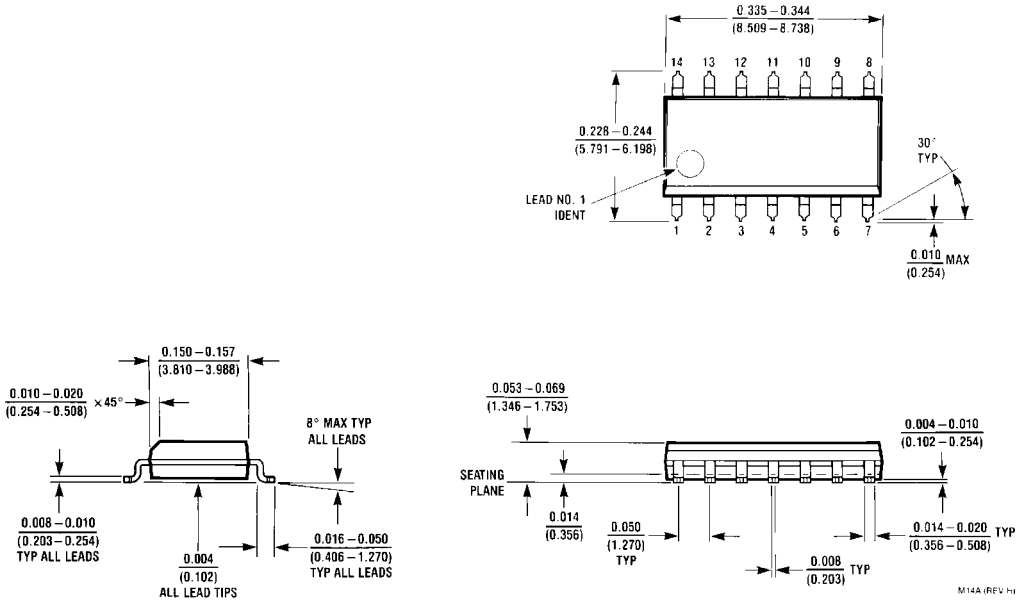
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Set-up Time, HIGH or LOW D_n to CP_n	5.0	1.0	3.0	3.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP_n	5.0	–0.5	1.0	1.0	ns
t_W	CP_n or $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ Pulse Width	5.0	3.0	5.0	6.0	ns
t_{rec}	Recovery Time $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP	5.0	–2.5	0	0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

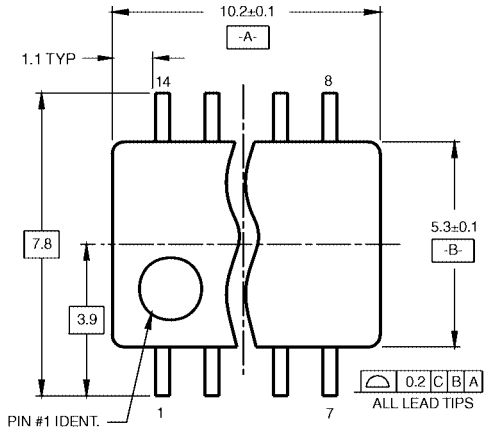
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	35.0	pF	V_{CC} = 5.0V

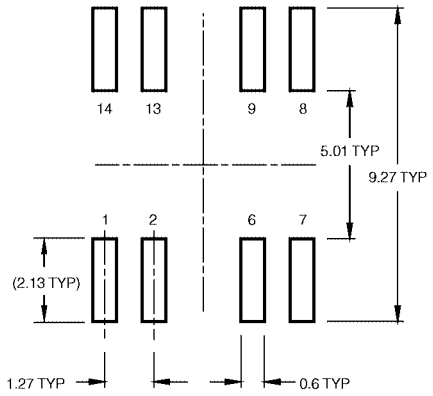
Physical Dimensions inches (millimeters) unless otherwise noted



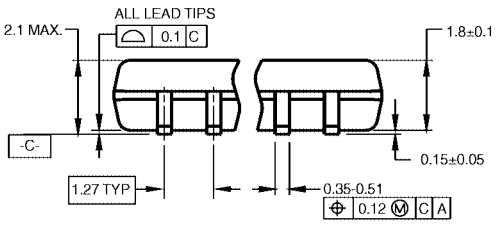
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

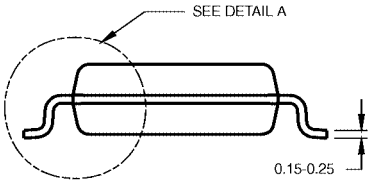
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



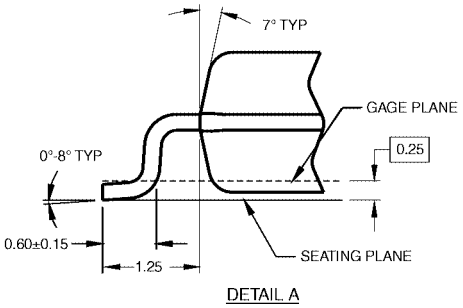


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

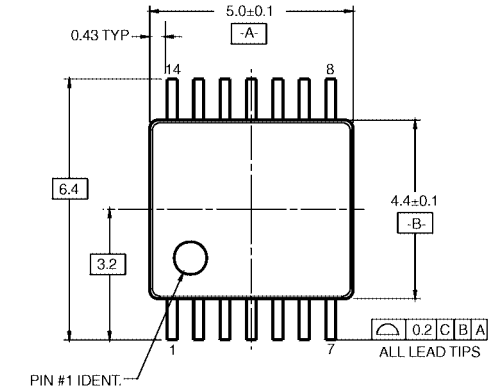
B. DIMENSIONS ARE IN MILLIMETERS.

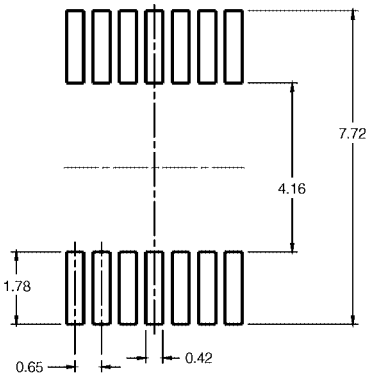
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





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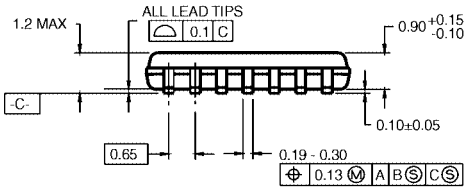
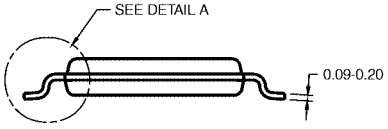
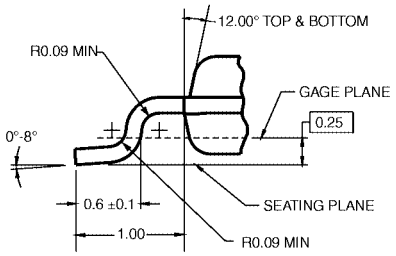






DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

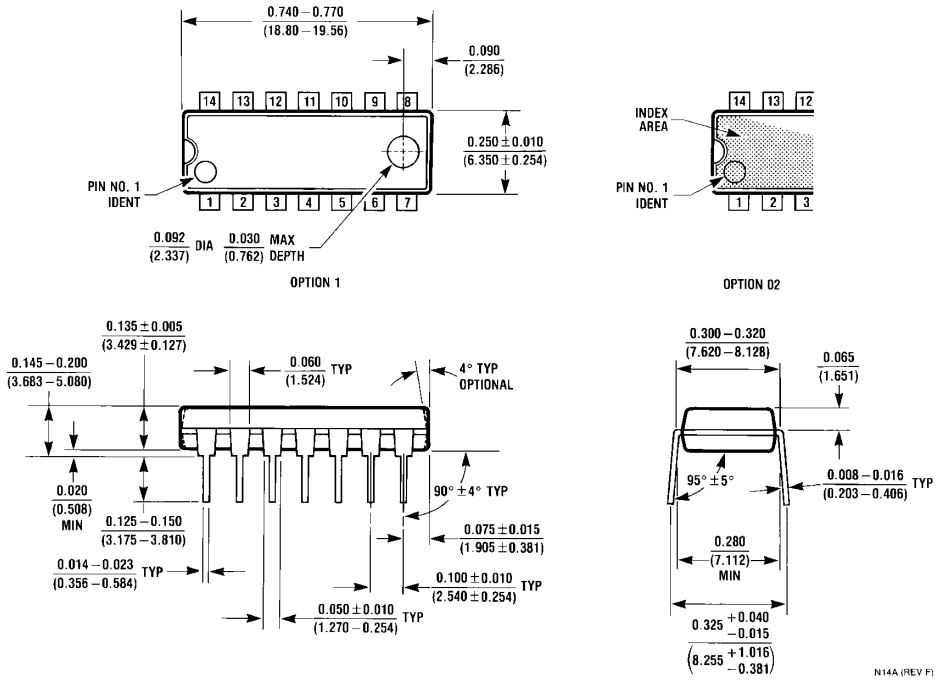
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised December 1998

74AC821 • 74ACT821
10-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The AC/ACT821 is a 10-bit D-type flip-flop with 3-STATE outputs arranged in a broadside pinout.

The AC/ACT821 is functionally identical to the AM29821.

Features

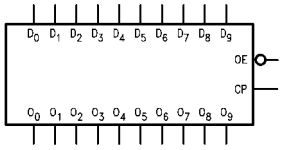
- 3-STATE outputs for bus interfacing
- Noninverting outputs
- Outputs source/sink 24 mA
- ACT821 has TTL-compatible inputs

Ordering Code:

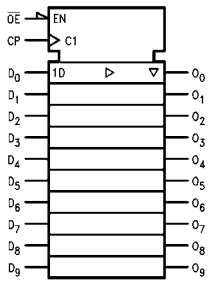
Order Number	Package Number	Package Description
74AC821SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74AC821SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300” Wide
74ACT821SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACT821MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT821SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code. (SPC not available in Tape and Reel.)

Logic Symbols

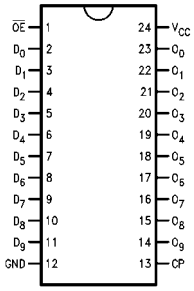


IEEE/IEC



Connection Diagram

Pin Assignment for DIP, SOIC and TSSOP



Pin Descriptions

Pin Names	Description
D_0–D_9	Data Inputs
O_0–O_9	Data Outputs
$\overline{OE}$	Output Enable Input
CP	Clock Input

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The AC/ACT821 consists of ten D-type edge-triggered flip-flops. The buffered Clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW the contents of the flip-flops are available at the outputs. When $\overline{OE}$ is HIGH the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

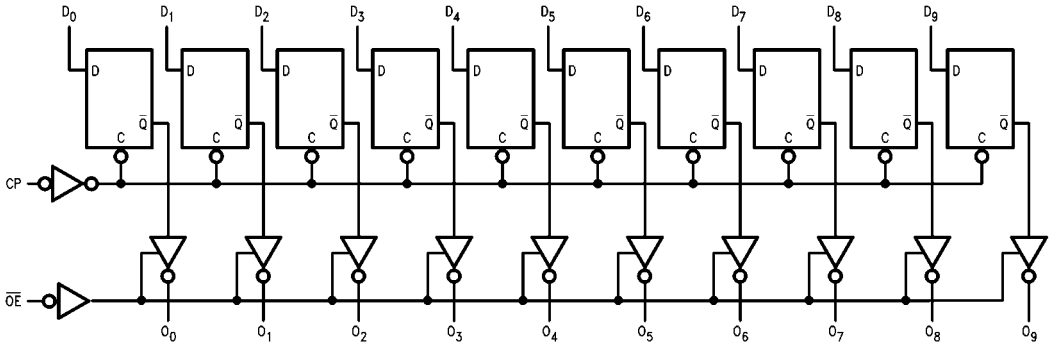
The AC/ACT821 is functionally and pin compatible with the AM29821.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	⌐	L	L	Z	High Z
H	⌐	H	H	Z	High Z
L	⌐	L	L	L	Load
L	⌐	H	H	H	Load

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	− 0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	− 20 mA
V_I = V_{CC} + 0.5V	+ 20 mA
DC Input Voltage (V_I)	− 0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	− 20 mA
V_O = V_{CC} + 0.5V	+ 20 mA
DC Output Voltage (V_O)	− 0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	− 65°C to + 150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
AC	2.0V to 6.0V
ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	− 40°C to + 85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		I_{OUT} = − 50 µA
	Output Voltage	4.5	4.49	4.4	4.4	V	
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = − 12 mA
		4.5		3.86	3.76	V	I_{OH} = − 24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		I_{OUT} = 50 µA
	Output Voltage	4.5	0.001	0.1	0.1	V	
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	µA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76		$I_{OH} = -24$ mA
		5.5		4.86	4.76	V	$I_{OH} = -24$ mA (Note 5)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44		$I_{OL} = 24$ mA
		5.5		0.36	0.44	V	$I_{OL} = 24$ mA (Note 5)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 6)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	$V_{IN} = V_{CC}$ or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{max}	Maximum Clock Frequency	3.3	110	145		100		MHz
		5.0	120	160		110		
t_{PLH}	Propagation Delay CP to O_n	3.3	3.0	8.0	13.0	3.0	15.0	ns
		5.0	2.0	6.0	9.5	2.0	10.5	
t_{PHL}	Propagation Delay CP to O_n	3.3	3.0	8.0	13.0	3.0	15.0	ns
		5.0	2.0	5.5	9.5	2.0	10.5	
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	3.3	2.5	6.0	11.0	2.5	12.0	ns
		5.0	1.5	4.5	8.0	1.5	9.0	
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	3.3	2.5	6.5	11.0	2.5	12.0	ns
		5.0	1.5	5.0	8.0	1.5	9.0	
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	3.3	2.5	6.5	10.5	2.5	11.0	ns
		5.0	1.5	5.0	8.0	1.5	8.5	
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	3.3	2.5	6.0	10.5	2.5	11.0	ns
		5.0	1.5	4.5	8.0	1.5	8.5	

Note 7: Voltage Range 3.3 is 3.3V ± 0.3V
Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	−1.0	1.5	1.5	ns
	D_n to CP	5.0	−1.0	1.5	1.5	
t_H	Hold Time, HIGH or LOW	3.3	−1.0	3.5	4.0	ns
	D_n to CP	5.0	−1.0	3.5	4.0	
t_W	CP Pulse Width	3.3	3.5	5.0	5.5	ns
	HIGH or LOW	5.0	2.5	4.0	4.0	

Note 8: Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	5.0	120	150		110		MHz
t_{PLH}	Propagation Delay CP to O_n	5.0	2.0	6.0	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay CP to O_n	5.0	2.5	6.0	9.5	2.0	10.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	7.0	10.5	2.0	11.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	7.0	10.5	2.0	12.0	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	7.5	12.0	1.0	13.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	7.0	10.5	1.0	11.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements for ACT

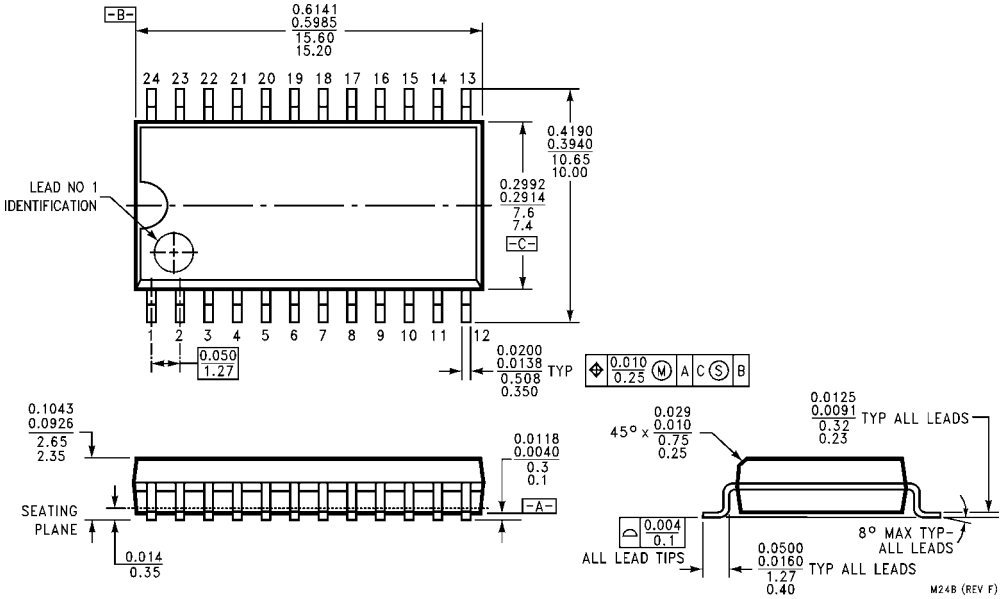
Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	2.5	2.0	2.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	−0.5	2.0	2.5	ns
t_W	CP Pulse Width HIGH or LOW	5.0	3.0	4.5	5.5	ns

Note 10: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

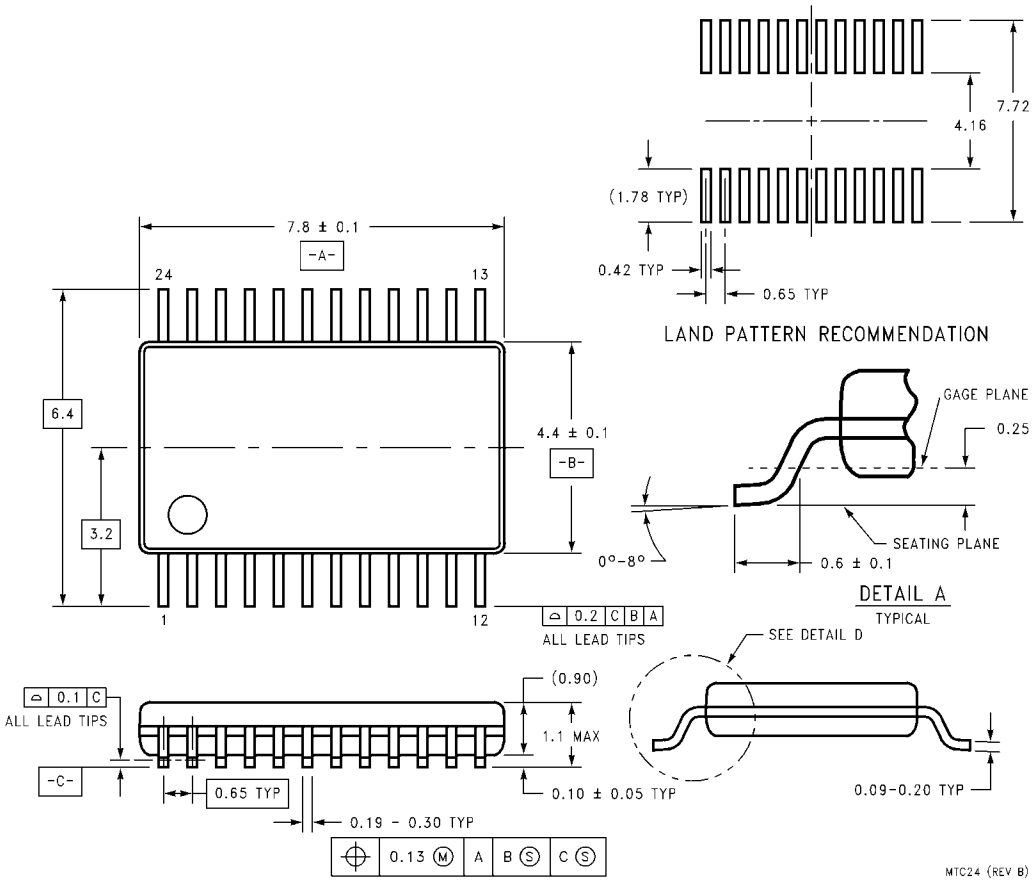
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	35.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



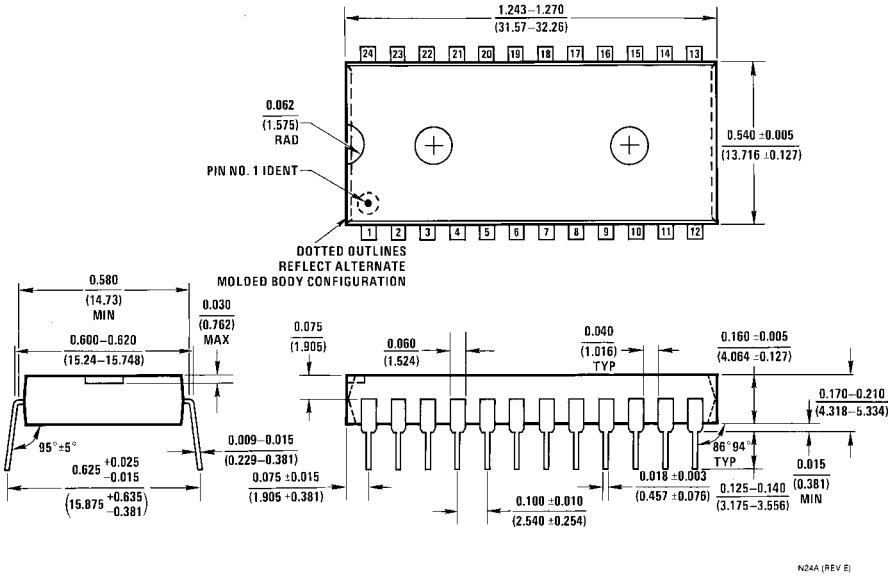
24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600" Wide
Package Number N24A

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

April 1993

74AC843 • 74ACT843
9-Bit Transparent Latch

General Description

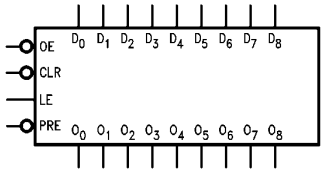
The 'AC/'ACT843 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths.

The 'AC/'ACT843 is functionally and pin compatible with AMD's Am29843.

Features

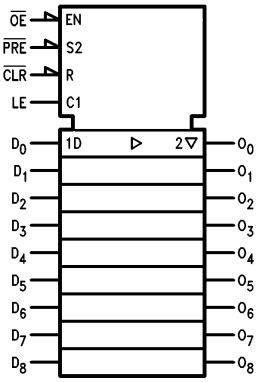
- 'ACT843 has TTL-compatible inputs
- TRI-STATE® outputs for bus interfacing

Logic Symbols



TL/F/9800–1

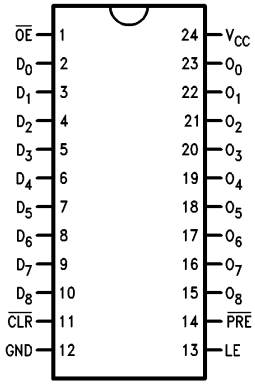
IEEE/IEC



TL/F/9800–3

Connection Diagram

Pin Assignment for DIP and SOIC



TL/F/9800–2

Pin Names	Description
D_0–D_8	Data Inputs
O_0–O_8	Data Outputs
$\overline{OE}$	Output Enable
LE	Latch Enable
$\overline{CLR}$	Clear
$\overline{PRE}$	Preset

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FACT™ is a trademark of National Semiconductor Corporation

RRD-B30M75/Printed in U. S. A.

Functional Description

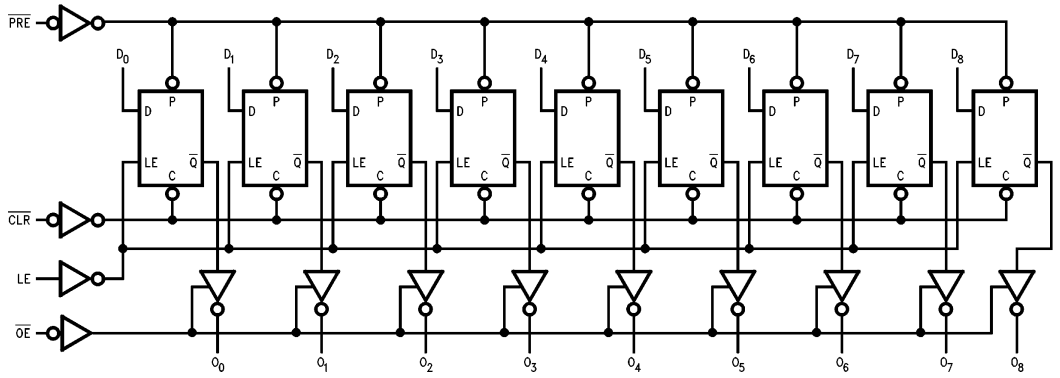
The ’AC/’ACT843 consists of nine D-type latches with TRI-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition. On the LE HIGH-to-LOW transition, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state. In addition to the LE and $\overline{OE}$ pins, the ’AC/’ACT843 has a Clear ($\overline{CLR}$) pin and a Preset ($\overline{PRE}$) pin. These pins are ideal for parity bus interfacing in high performance systems. When $\overline{CLR}$ is LOW, the outputs are LOW if $\overline{OE}$ is LOW. When $\overline{CLR}$ is HIGH, data can be entered into the latch. When $\overline{PRE}$ is LOW, the outputs are HIGH if $\overline{OE}$ is LOW. Preset overrides $\overline{CLR}$.

Function Tables

Inputs					Internal	Outputs	Function
$\overline{CLR}$	$\overline{PRE}$	$\overline{OE}$	LE	D	Q	O	
H	H	H	H	L	L	Z	High Z
H	H	H	H	H	H	Z	High Z
H	H	H	L	X	NC	Z	Latched
H	H	L	H	L	L	L	Transparent
H	H	L	H	H	H	H	Transparent
H	H	L	L	X	NC	NC	Latched
H	L	L	X	X	H	H	Preset
L	H	L	X	X	L	L	Clear
L	L	L	X	X	H	H	Preset
L	H	H	L	X	L	Z	Clear/High Z
H	L	H	L	X	H	Z	Preset/High Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



TL/F/9800–5

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74AC/ACT	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

DC Electrical Characteristics for 'AC Family Devices

Symbol	Parameter	V_{CC} (V)	74AC		74AC	Units	Conditions
			$T_A = +25°C$		$T_A = -40°C$ to $+85°C$		
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	$I_{OUT} = -50\ \mu A$
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
		3.0		2.56	2.46	V	*$V_{IN} = V_{IL}$ or V_{IH} I_{OH} −12 mA
		4.5		3.86	3.76		I_{OH} −24 mA
		5.5		4.86	4.76		I_{OH} −24 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
		3.0		0.36	0.44	V	*$V_{IN} = V_{IL}$ or V_{IH} I_{OL} 12 mA
		4.5		0.36	0.44		I_{OL} 24 mA
		5.5		0.36	0.44		I_{OL} 24 mA
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND

*All outputs loaded; thresholds on input associated with output under test.

DC Electrical Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V_{CC} (V)	74AC $T_A = +25°C$		74AC $T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits			
I_{OZ}	Maximum TRI-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	†Minimum Dynamic Output Current	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

DC Electrical Characteristics for 'ACT Family Devices

Symbol	Parameter	V_{CC} (V)	74ACT $T_A = +25°C$		74ACT $T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	*V_{IN} = V_{IL} or V_{IH} I_{OH} −24 mA −24 mA
V_{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	*V_{IN} = V_{IL} or V_{IH} I_{OL} 24 mA 24 mA
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum TRI-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	†Minimum Dynamic Output Current	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF			74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to O_n	3.3	3.5	6.5	12.0	2.5	13.0	ns
		5.0	2.0	4.5	8.5	1.5	9.0	
t_{PHL}	Propagation Delay D_n to O_n	3.3	4.0	7.0	12.0	3.0	13.0	ns
		5.0	2.5	5.0	8.5	1.5	9.0	
t_{PLH}	Propagation Delay LE to O_n	3.3	3.5	6.5	12.0	13.0	2.5	ns
		5.0	2.0	4.5	8.5	1.5	9.0	
t_{PHL}	Propagation Delay LE to O_n	3.3	4.0	7.0	12.0	3.0	13.0	ns
		5.0	2.5	5.0	8.5	1.5	9.0	
t_{PLH}	Propagation Delay $\overline{PRE}$ to O_n	3.3	5.5	8.5	19.0	4.5	21.5	ns
		5.0	3.5	6.0	13.0	2.5	14.5	
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	3.3	7.5	11.0	21.5	6.0	24.0	ns
		5.0	5.0	7.5	15.0	4.0	17.0	
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	3.3	3.5	6.0	11.0	3.0	12.0	ns
		5.0	2.0	4.5	8.0	1.5	9.0	
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	3.3	4.0	6.5	11.0	2.5	12.0	ns
		5.0	2.0	5.0	8.0	1.5	9.0	
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	3.3	4.0	6.5	10.5	3.5	11.0	ns
		5.0	3.0	5.0	8.0	2.5	8.5	
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	3.3	3.0	6.0	10.5	2.5	11.0	ns
		5.0	2.0	4.5	8.0	1.5	8.5	
t_{PHL}	Propagation Delay $\overline{PRE}$ to O_n	3.3	4.5	7.0	12.5	3.5	13.5	ns
		5.0	3.0	5.0	9.0	2.0	9.5	
t_{PLH}	Propagation Delay $\overline{CLR}$ to O_n	3.3	4.5	7.0	12.5	3.5	13.5	ns
		5.0	3.0	5.0	9.0	2.0	9.5	

*Voltage Range 3.3 is 3.3V ±0.3V

*Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF		74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_s	Setup Time, HIGH or LOW D_n to LE	3.3 5.0	0 −0.5	3.0 1.5	3.5 2.0	ns
t_h	Hold Time, HIGH or LOW D_n to LE	3.3 5.0	 −0.5	2.0 2.5	2.0 2.5	ns
t_w	LE Pulse Width, HIGH	3.3 5.0	1.5 1.5	3.0 3.0	3.0 3.0	ns
t_w	$\overline{PRE}$ Pulse Width, LOW	3.3 5.0	5.0 3.0	12.0 8.5	14.5 10.0	ns
t_w	$\overline{CLR}$ Pulse Width, LOW	3.3 5.0	5.5 4.0	14.0 10.0	16.5 12.0	ns
t_{rec}	$\overline{PRE}$ Recovery Time	3.3 5.0	1.0 0	3.0 1.5	3.0 1.5	ns
t_{rec}	$\overline{CLR}$ Recovery Time	3.3 5.0	0 −0.5	1.5 0.5	1.5 0.5	ns

*Voltage Range 3.3 is 3.3V ±0.3V

*Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics

Symbol	Parameter	V_{CC}* (V)	74ACT $T_A = +25°C$, $C_L = 50$ pF			74ACT $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to O_n	5.0	2.5	5.5	9.5	2.0	10.0	ns
t_{PHL}	Propagation Delay D_n to O_n	5.0	2.5	5.5	9.5	2.0	10.0	ns
t_{PLH}	Propagation Delay LE to O_n	5.0	2.5	5.5	9.0	2.0	10.0	ns
t_{PHL}	Propagation Delay LE to O_n	5.0	2.5	5.5	9.0	2.0	10.0	ns
t_{PLH}	Propagation Delay $\overline{PRE}$ to O_n	5.0	2.5	6.5	14.0	2.0	16.0	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	7.5	15.5	2.0	17.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	2.5	6.0	10.5	2.0	11.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	2.5	6.0	10.5	2.0	11.0	ns
t_{PHL}	Propagation Delay $\overline{PRE}$ to O_n	5.0	2.5	6.0	10.5	2.0	11.0	ns
t_{PLH}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns

*Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF		74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_s	Setup Time, HIGH or LOW D_n to LE	5.0	−0.5	0.5	1.0	ns
t_h	Hold Time, HIGH or LOW D_n to LE	5.0	0.5	2.0	2.0	ns
t_w	LE Pulse Width, HIGH	5.0	2.0	3.5	3.5	ns
t_w	$\overline{PRE}$ Pulse Width, LOW	5.0	5.0	8.5	10.0	ns
t_w	$\overline{CLR}$ Pulse Width, LOW	5.0	5.5	9.5	11.0	ns
t_{rec}	$\overline{PRE}$ Recovery Time	5.0	0.5	2.0	2.0	ns
t_{rec}	$\overline{CLR}$ Recovery Time	5.0	−0.5	1.0	1.0	ns

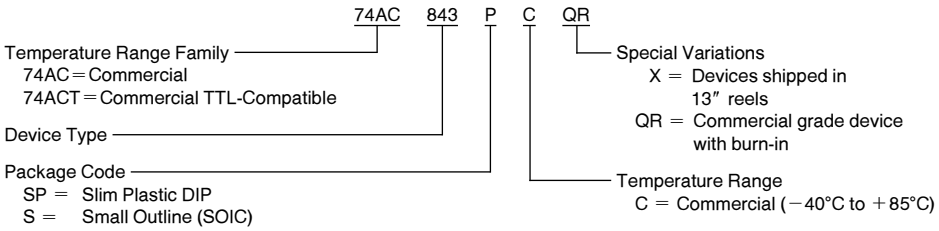
*Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

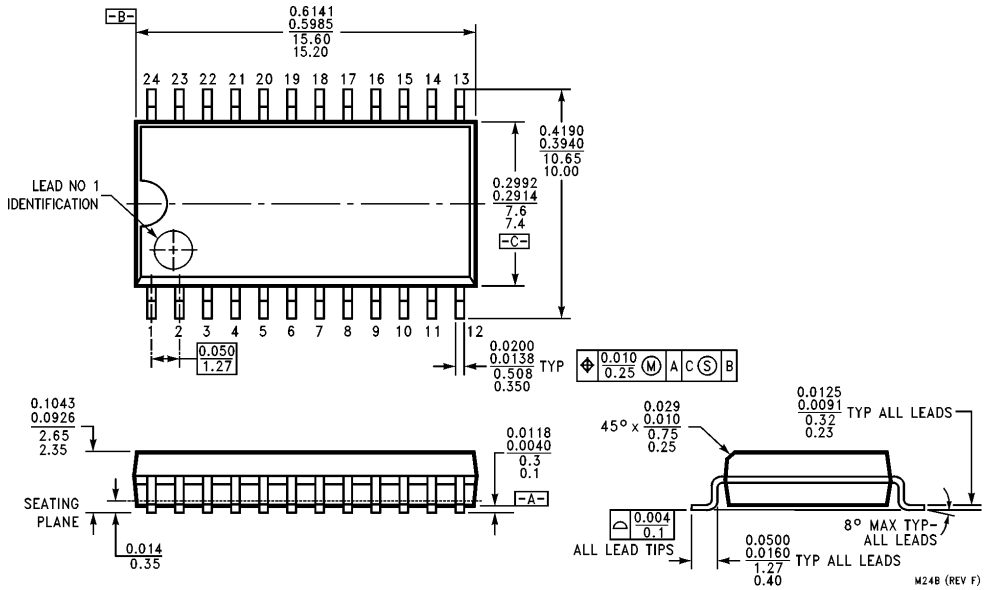
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	44	pF	V_{CC} = 5.0V

Ordering Information

The device number is used to form part of a simplified purchasing code where a package type and temperature range are defined as follows:



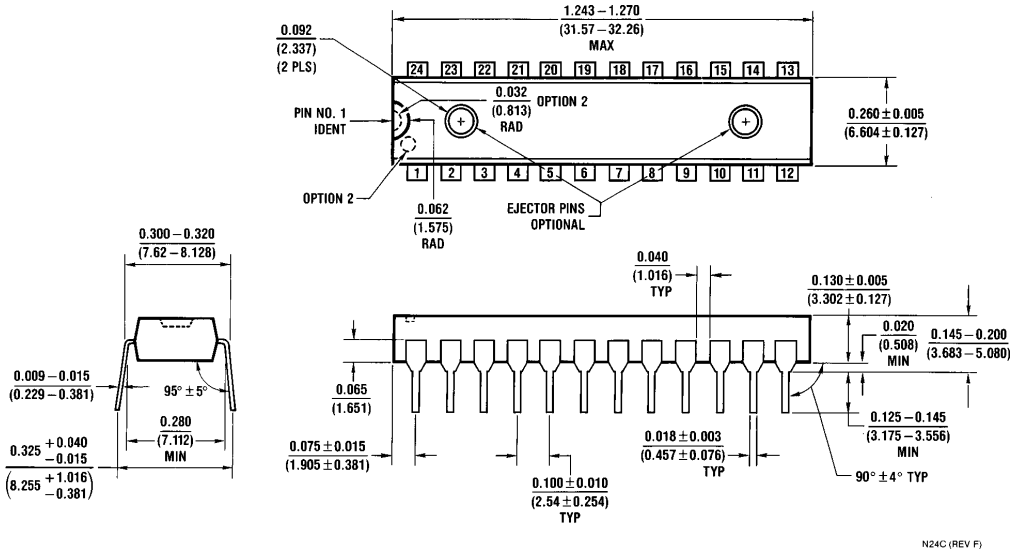
Physical Dimensions inches (millimeters)



24-Lead Small Outline Integrated Circuit (S)
NS Package Number M24B

Physical Dimensions inches (millimeters) (Continued)

Lit. # 114638



24-Lead Slim (0.300″ Wide) Plastic Dual-In-Line Package (SP)
NS Package Number N24C

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

September 1988
Revised November 1999

74AC86
Quad 2-Input Exclusive-OR Gate

General Description

The AC86 contains four, 2-input exclusive-OR gates.

Features

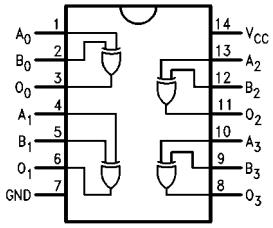
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA

Ordering Code:

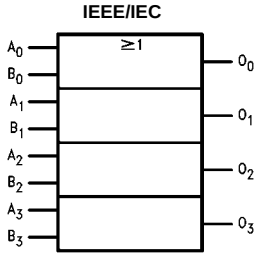
Order Number	Package Number	Package Description
74AC86SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74AC86SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC86PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names	Description
A_0–A_3	Inputs
B_0–B_3	Inputs
O_0–O_3	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = 0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = 25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 20 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

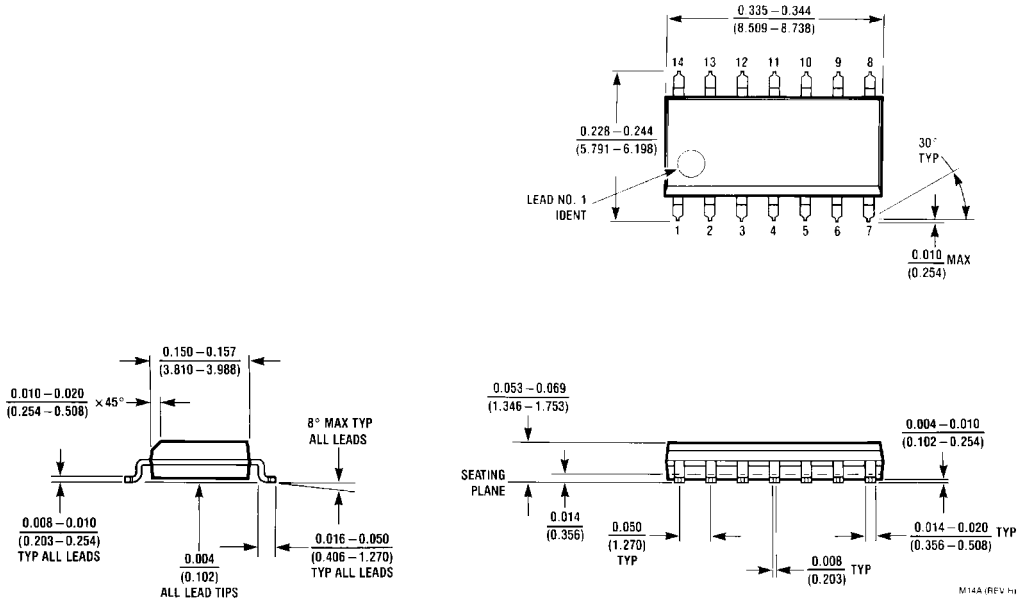
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, C_L 40 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.0	6.0	11.5	1.5	12.5	ns
	Inputs to Outputs	5.0	1.5	4.5	8.5	1.0	9.5	
t_{PLH}	Propagation Delay	3.3	2.0	6.5	11.5	1.5	12.5	ns
	Inputs to Outputs	5.0	1.5	4.5	8.5	1.0	9.0	

Note 5: Voltage Range 3.3V is 3.3V ± 0.3V
Voltage Range 5.0V is 5.0V ± 0.5V

Capacitance

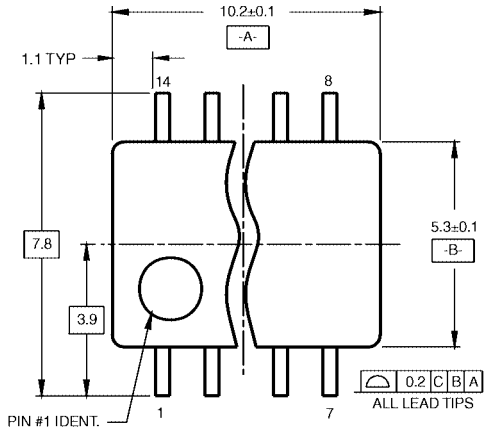
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	35	pF	V_{CC} = 5.0V

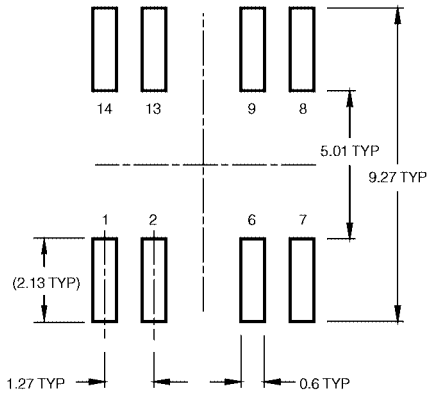
Physical Dimensions inches (millimeters) unless otherwise noted



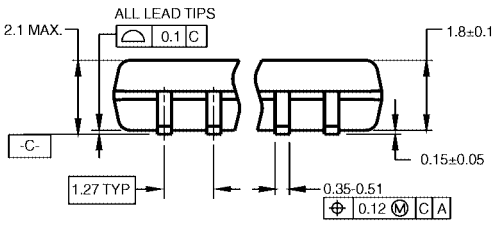
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number M14A

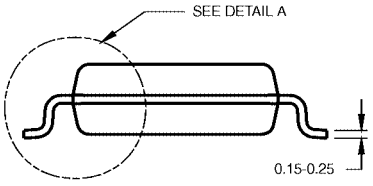
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



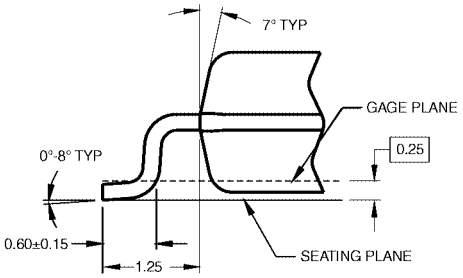


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

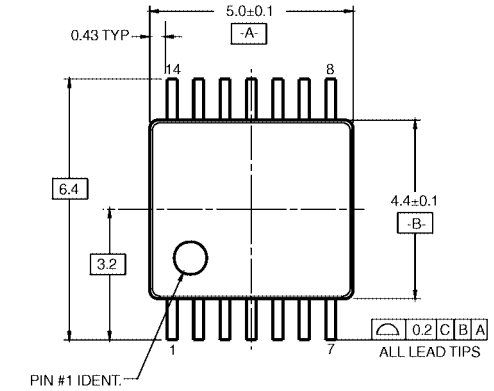
B. DIMENSIONS ARE IN MILLIMETERS.

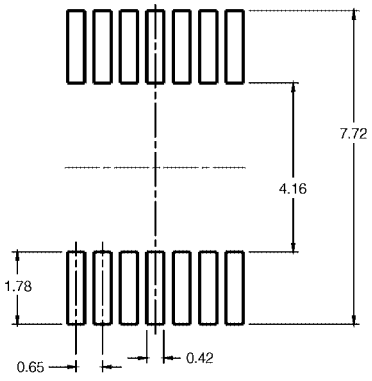
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

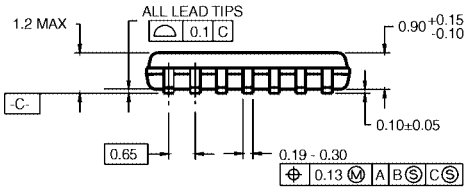
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

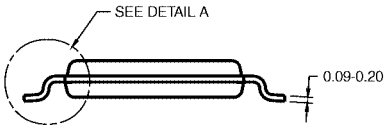
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





NOTES:

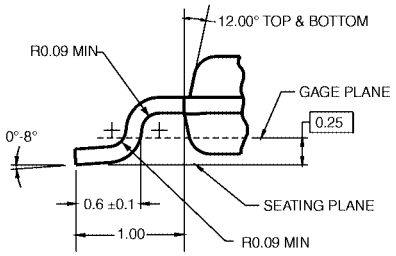
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

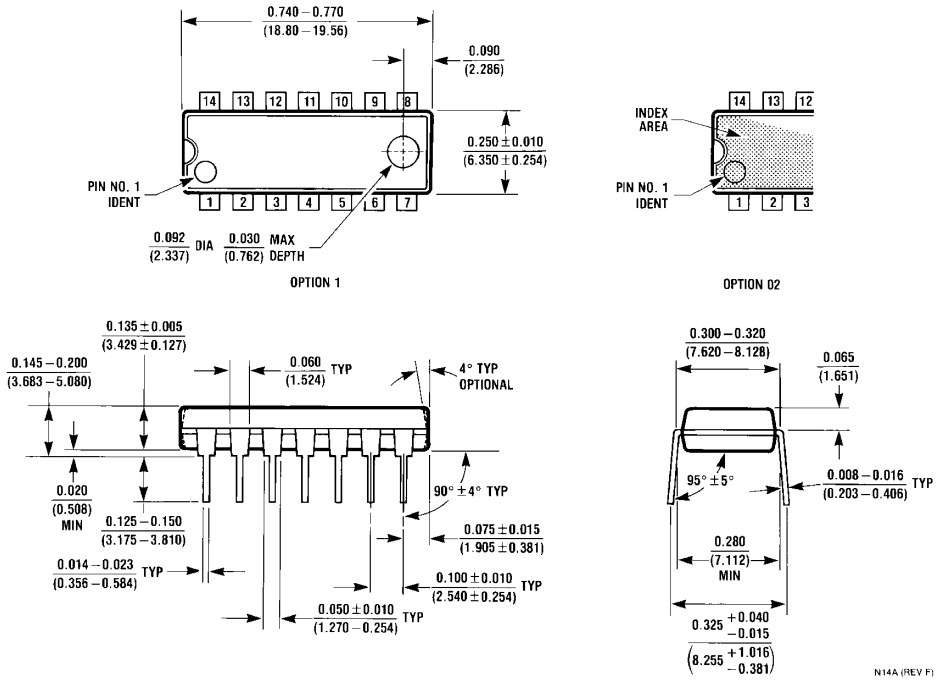
MTC14RevC3



DETAIL A

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1998

74ACT899
9-Bit Latchable Transceiver with Parity Generator/Checker

General Description

The ACT899 is a 9-bit to 9-bit parity transceiver with transparent latches. The device can operate as a feed-through transceiver or it can generate/check parity from the 8-bit data busses in either direction. The ACT899 features independent latch enables for the A-to-B direction and the B-to-A direction, a select pin for ODD/$\overline{\text{EVEN}}$ parity, and separate error signal output pins for checking parity.

Features

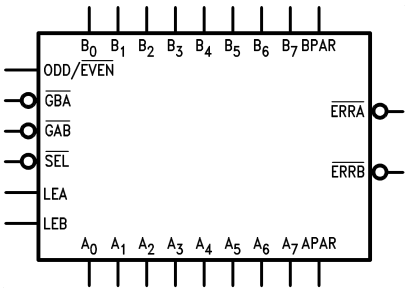
- Latchable transceiver with output sink of 24 mA
- Option to select generate parity and check or "feed-through" data/parity in directions A-to-B or B-to-A
- Independent latch enable for A-to-B and B-to-A directions
- Select pin for ODD/$\overline{\text{EVEN}}$ parity
- $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ output pins for parity checking
- Ability to simultaneously generate and check parity
- May be used in system applications in place of the 280
- May be used in system applications in place of the 657 and 373 (no need to change T/$\overline{\text{R}}$ to check parity)
- 4 kV minimum ESD immunity

Ordering Code:

Order Number	Package Number	Package Description
74ACT899QC	V28A	28-Lead Molded Chip Carrier

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

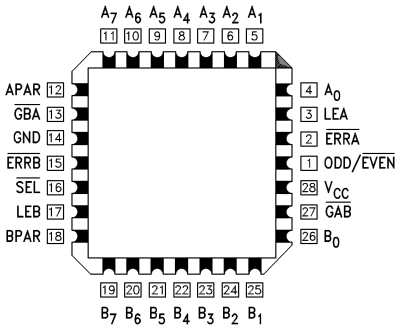
Logic Symbol



DS010637-1

Connection Diagram

Pin Assignment for PCC



DS010637-2

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Pin Descriptions

Pin Names	Description
A_0–A_7	A Bus Data Inputs/Data Outputs
B_0–B_7	B Bus Data Inputs/Data Outputs
APAR, BPAR	A and B Bus Parity Inputs
ODD/$\overline{\text{EVEN}}$	ODD/$\overline{\text{EVEN}}$ Parity Select, Active LOW for EVEN Parity
$\overline{\text{GBA}}$, $\overline{\text{GAB}}$	Output Enables for A or B Bus, Active LOW
$\overline{\text{SEL}}$	Select Pin for Feed-Through or Generate Mode, LOW for Generate Mode
LEA, LEB	Latch Enables for A and B Latches, HIGH for Transparent Mode
$\overline{\text{ERRA}}$, $\overline{\text{ERRB}}$	Error Signals for Checking Generated Parity with Parity In, LOW if Error Occurs

Functional Description

The ACT899 has three principal modes of operation which are outlined below. These modes apply to both the A-to-B and B-to-A directions.

- Bus A (B) communicates to Bus B (A), parity is generated and passed on to the B (A) Bus as BPAR (APAR). If LEB (LEA) is HIGH and the Mode Select ($\overline{\text{SEL}}$) is LOW, the parity generated from B[0:7] (A[0:7]) can be checked and monitored by $\overline{\text{ERRB}}$ ($\overline{\text{ERRA}}$).
- Bus A (B) communicates to Bus B (A) in a feed-through mode if $\overline{\text{SEL}}$ is HIGH. Parity is still generated and checked as $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ in the feed-through mode (can be used as an interrupt to signal a data/parity bit error to the CPU).
- Independent Latch Enables (LEA and LEB) allow other permutations of generating/checking (see Function Table).

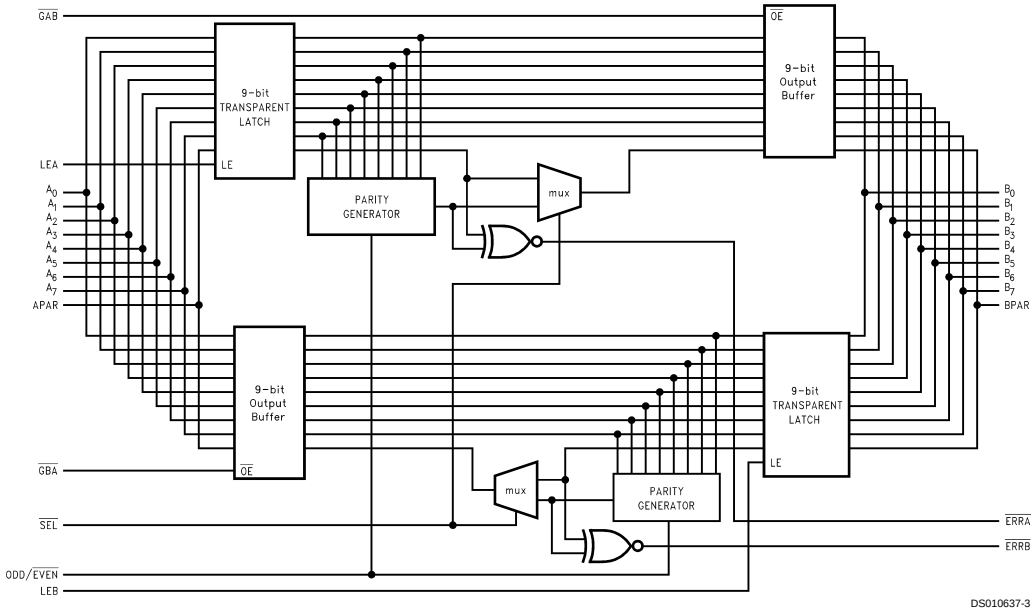
Function Table

Inputs					Operation
$\overline{\text{GAB}}$	$\overline{\text{GBA}}$	$\overline{\text{SEL}}$	LEA	LEB	
H	H	X	X	X	Busses A and B are 3-STATE.
H	L	L	L	H	Generates parity from B[0:7] based on O/$\overline{\text{E}}$ (Note 1). Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$.
H	L	L	H	H	Generates parity from B[0:7] based on O/$\overline{\text{E}}$. Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$. Generated parity also fed back through the A latch for generate/check as $\overline{\text{ERRA}}$.
H	L	L	X	L	Generates parity from B latch data based on O/$\overline{\text{E}}$. Generated parity → APAR. Generated parity checked against latched BPAR and output as $\overline{\text{ERRB}}$.
H	L	H	X	H	BPAR/B[0:7] → APAR/A0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$.
H	L	H	H	H	BPAR/B[0:7] → APAR/A[0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$. Generated parity also fed back through the A latch for generate/check as $\overline{\text{ERRA}}$.
L	H	L	H	L	Generates parity for A[0:7] based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$.
L	H	L	H	H	Generates parity from A[0:7] based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$. Generated parity also fed back through the B latch for generate/check as $\overline{\text{ERRB}}$.
L	H	L	L	X	Generates parity from A latch data based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against latched APAR and output as $\overline{\text{ERRA}}$.
L	H	H	H	L	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$.
L	H	H	H	H	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$. Generated parity also fed back through the B latch for generate/check as $\overline{\text{ERRB}}$.

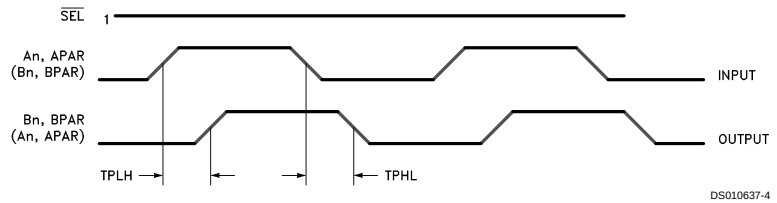
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Note 1: O/$\overline{\text{E}}$ = ODD/$\overline{\text{EVEN}}$

Functional Block Diagram

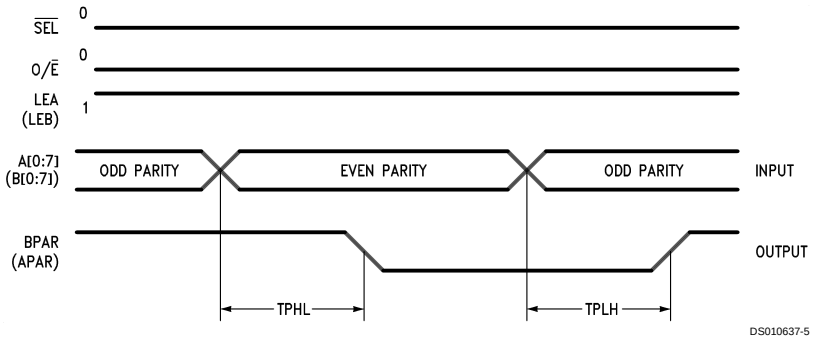


AC Path



A_n, APAR → B_n, BPAR
(B_n, BPAR → A_n, APAR)

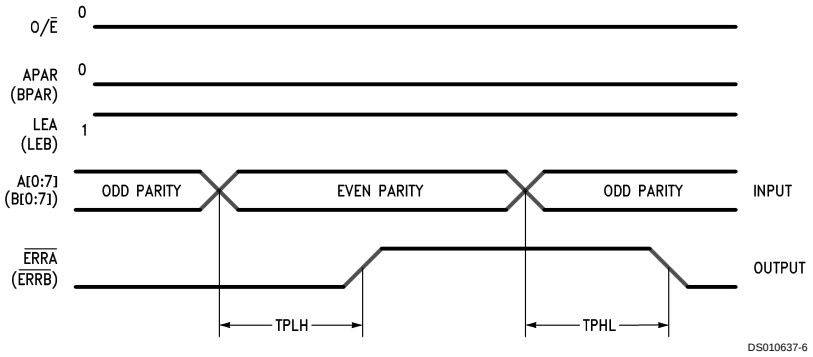
FIGURE 1.



A_n → BPAR
(B_n → APAR)

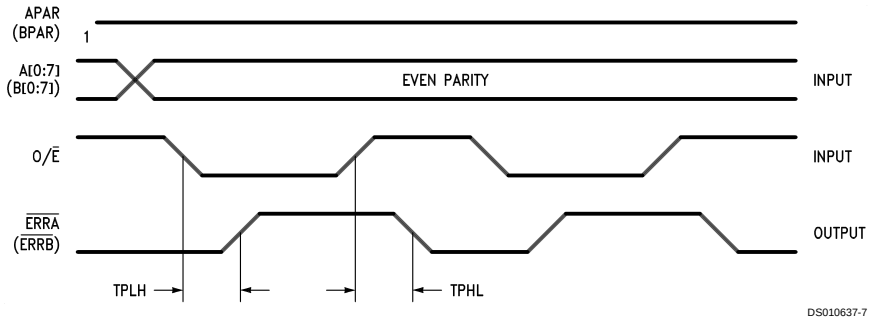
FIGURE 2.

AC Path (Continued)



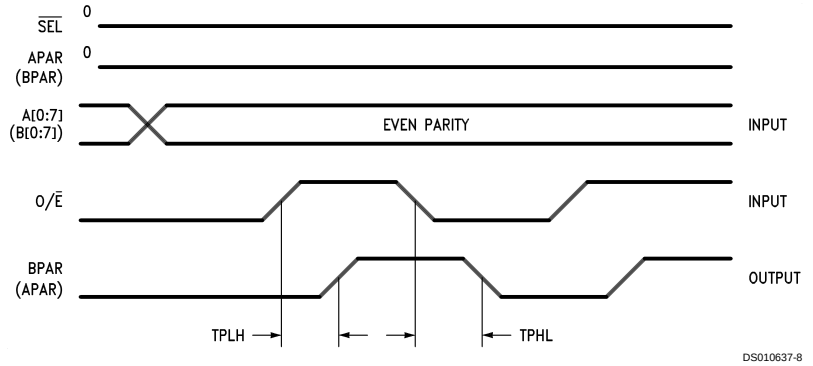
$A_n \rightarrow \overline{ERRA}$
$(B_n \rightarrow \overline{ERRB})$

FIGURE 3.



$O/\overline{E} \rightarrow \overline{ERRA}$
$O/\overline{E} \rightarrow \overline{ERRB}$

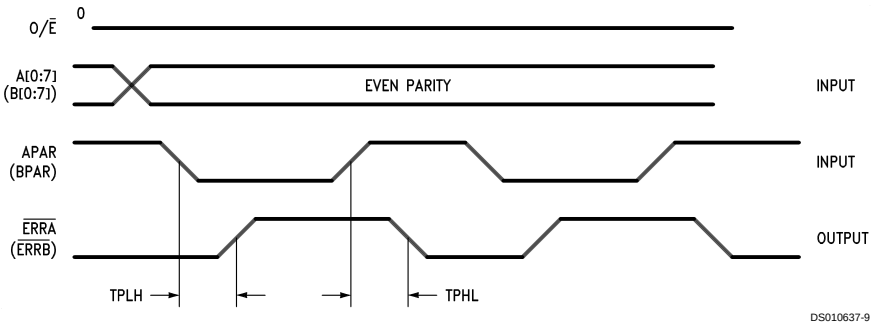
FIGURE 4.



$O/\overline{E} \rightarrow BPAR$
$(O/\overline{E} \rightarrow APAR)$

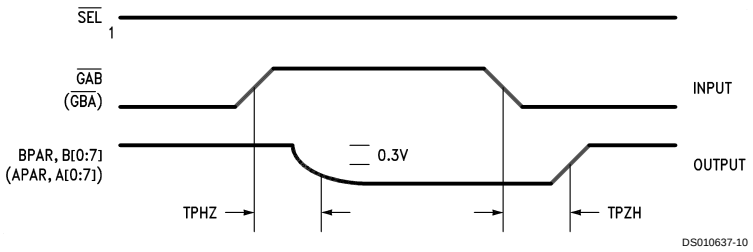
FIGURE 5.

AC Path (Continued)



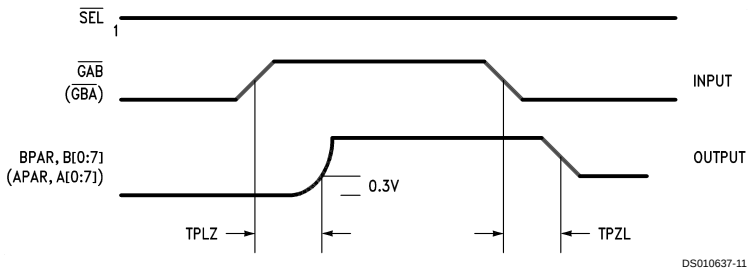
APAR → $\overline{ERRA}$
(BPAR → $\overline{ERRB}$)

FIGURE 6.



ZH, HZ

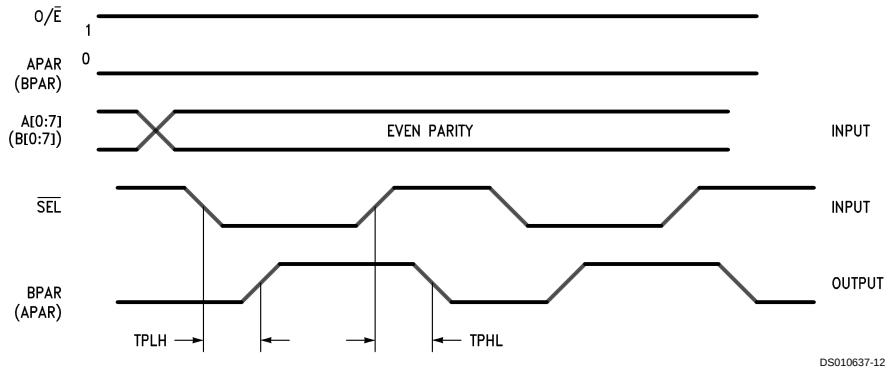
FIGURE 7.



ZL, LZ

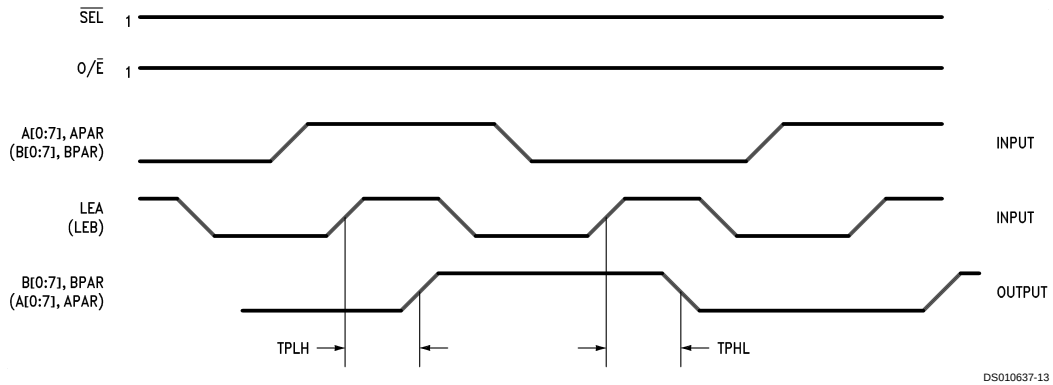
FIGURE 8.

AC Path (Continued)



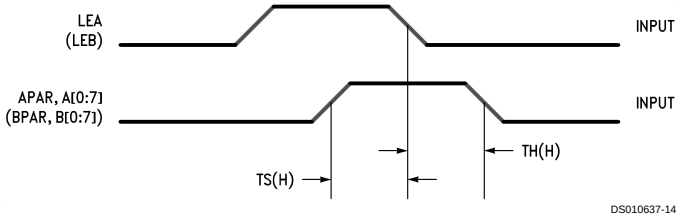
$\overline{SEL}$ → BPAR
($\overline{SEL}$ → APAR)

FIGURE 9.



LEA → BPAR, B[0:7]
(LEB → APAR, A[0:7])

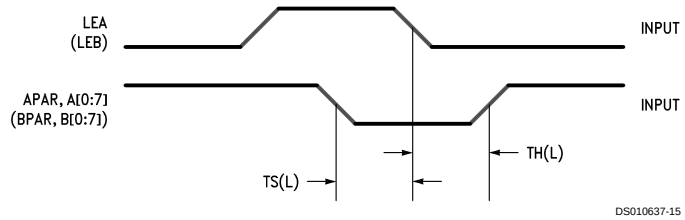
FIGURE 10.



TS(H), TH(H)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 11.

AC Path (Continued)



TS(L), TH(L)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 12.

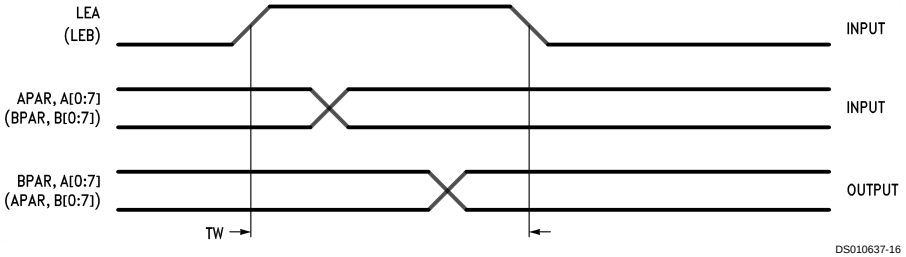


FIGURE 13.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140˚C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate $\Delta V/\Delta t$	125 mV/ns
V_{IN} from 0.8V to 2.0V V_{CC} @ 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 µA
		4.5 5.5		3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 µA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 3)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	µA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 4)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	V_{IN} = V_{CC} or GND

Note 3: Maximum of 9 outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25^\circ C$, $C_L = 50$ pF			$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to B_n, A_n	5.0	2.5	7.5	11.5	2.5	12.0	ns
t_{PLH} t_{PHL}	Propagation Delay APAR, BPAR to BPAR, APAR	5.0	1.5	6.0	8.5	1.5	9.0	ns
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to BPAR, APAR	5.0	2.5	8.5	12.0	2.5	12.5	ns
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$	5.0	2.0	8.0	11.5	2.0	12.0	ns
t_{PLH} t_{PHL}	Propagation Delay ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$	5.0	2.0	8.0	11.5	2.0	12.0	ns
t_{PLH} t_{PHL}	Propagation Delay ODD/$\overline{EVEN}$ to APAR, BPAR	5.0	2.5	8.0	11.5	2.5	12.0	ns
t_{PLH} t_{PHL}	Propagation Delay APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$	5.0	1.5	7.5	10.5	1.5	11.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{SEL}$ to APAR, BPAR	5.0	1.5	6.5	9.0	1.5	9.5	ns
t_{PLH} t_{PHL}	Propagation Delay LEB to A_n, B_n	5.0	2.5	7.0	10.5	2.5	11.0	ns
t_{PLH} t_{PHL}	Propagation Delay LEA to APAR, BPAR	5.0	2.0	8.0	11.5	2.0	12.0	ns
t_{PLH} t_{PHL}	Propagation Delay LEA, LEB to $\overline{ERRA}$, $\overline{ERRB}$	5.0	2.5	8.0	11.5	2.5	12.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{GBA}$ or $\overline{GAB}$ to A_n, B_n	5.0	2.5	7.0	10.5	2.5	11.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{GBA}$ or $\overline{GAB}$ to BPAR or APAR	5.0	1.5	6.0	9.0	1.5	9.5	ns
t_{PHZ} t_{PHL}	Output Disable Time $\overline{GBA}$ or $\overline{GAB}$ to A_n, B_n	5.0	1.5	6.5	9.5	1.5	9.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{GBA}$ or $\overline{GAB}$ to BPAR, APAR	5.0	1.5	6.5	9.5	1.5	9.5	ns

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

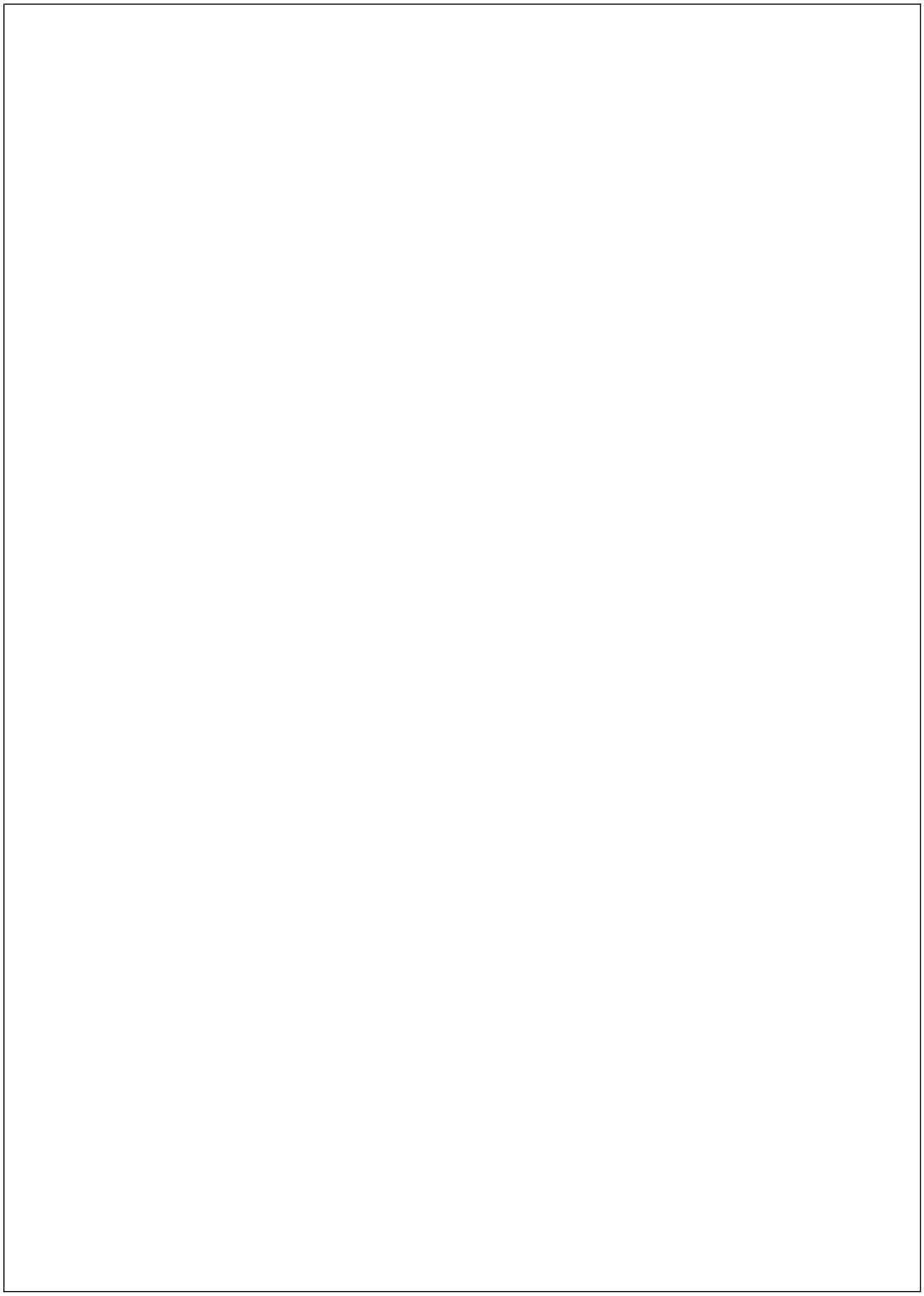
AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25^\circ C$, $C_L = 50$ pF	$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW A_n, B_n, PAR to LEA, LEB	5.0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW A_n, B_n, PAR to LEA, LEB	5.0	1.5	1.5	ns
t_W	Pulse Width for LEB, LEA	5.0	4.0	4.0	ns

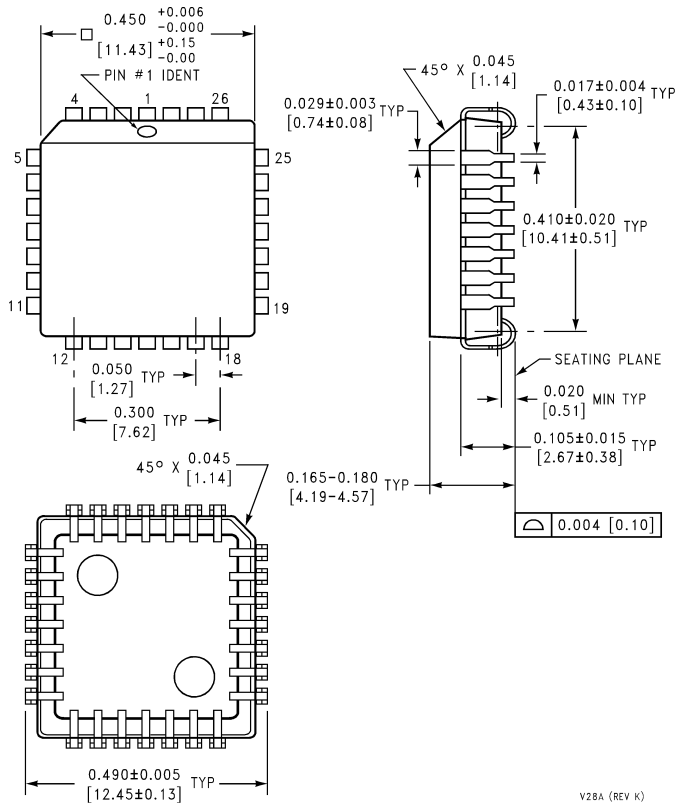
Note 6: Voltage Range 5.0 = 5.0V ± 0.5V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	210	pF	V_{CC} = 5.0V



Physical Dimensions inches (millimeters) unless otherwise noted



28-Lead Molded Chip Carrier
Package Number V28A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1989
Revised November 1999

74ACQ240 • 74ACTQ240
Quiet Series™ Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ACQ/ACTQ240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The ACQ/ACTQ utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

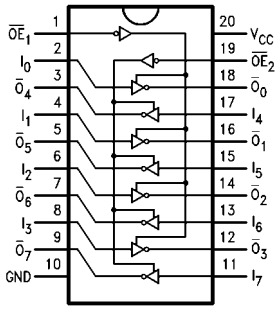
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- Inverting 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard ACT240

Ordering Code:

Order Number	Package Number	Package Description
74ACQ240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC)JEDEC MS-013, 0.300" Wide Body
74ACQ240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQ240PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACTQ240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC)JEDEC MS-013, 0.300" Wide Body
74ACTQ240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ240QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

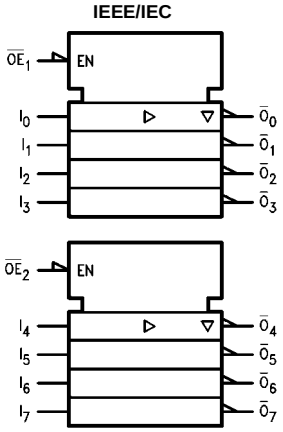
Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Logic Symbol



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: Plastic DIP package.

Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of data inputs (n) switching. (n −1) inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 8)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 9)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: Plastic DIP package.

Note 11: Max number of Data Inputs defined as (n). n−1 Data Inputs are driven 0V to 3V. One Data Input @ V_{IN} = GND.

Note 12: Max number of Data Inputs (n) switching. (n−1) Inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
		(Note 13)	Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.0	7.0	10.0	2.0	10.5	ns
t_{PLH}	Data to Output	5.0	1.5	5.0	6.5	1.5	7.0	
t_{PZL}	Output Enable Time	3.3	2.5	8.0	12.0	2.5	12.5	ns
t_{PZH}		5.0	1.5	5.5	8.0	1.5	8.5	
t_{PHZ}	Output Disable Time	3.3	1.0	8.5	13.5	1.0	14.0	ns
t_{PLZ}		5.0	1.0	6.0	9.0	1.0	9.5	
t_{OSHL}	Output to Output Skew	3.3		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output (Note 14)	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3 ± 0.3V.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
		(Note 15)	Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	1.5	5.5	7.0	1.5	7.5	ns
t_{PLH}	Data to Output							
t_{PZL}, t_{PZH}	Output Enable Time	5.0	1.5	6.5	8.5	1.5	9.0	ns
t_{PHZ}, t_{PLZ}	Output Disable Time	5.0	1.0	7.0	9.5	1.0	10.0	ns
t_{OSHL}	Output to Output Skew	5.0		0.5	1.0		1.0	ns
t_{OSLH}	Data to Output (Note 16)							

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Note 16: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

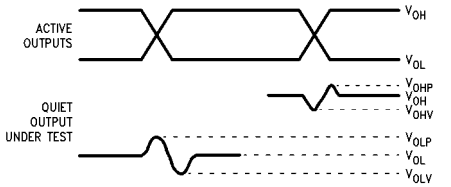
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 17: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 18: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

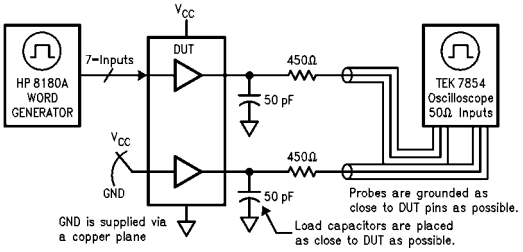
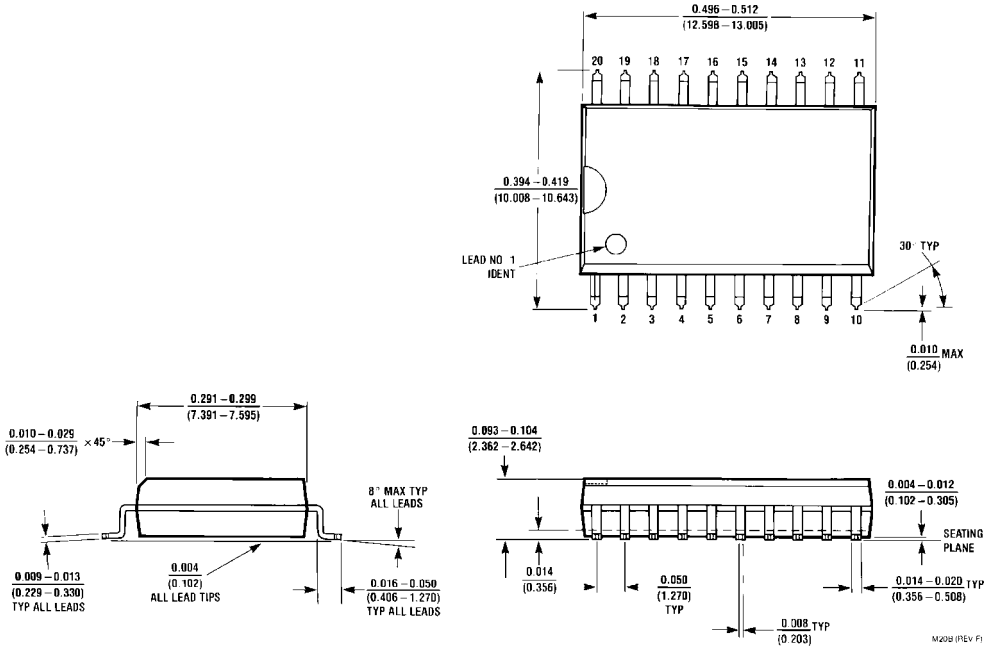


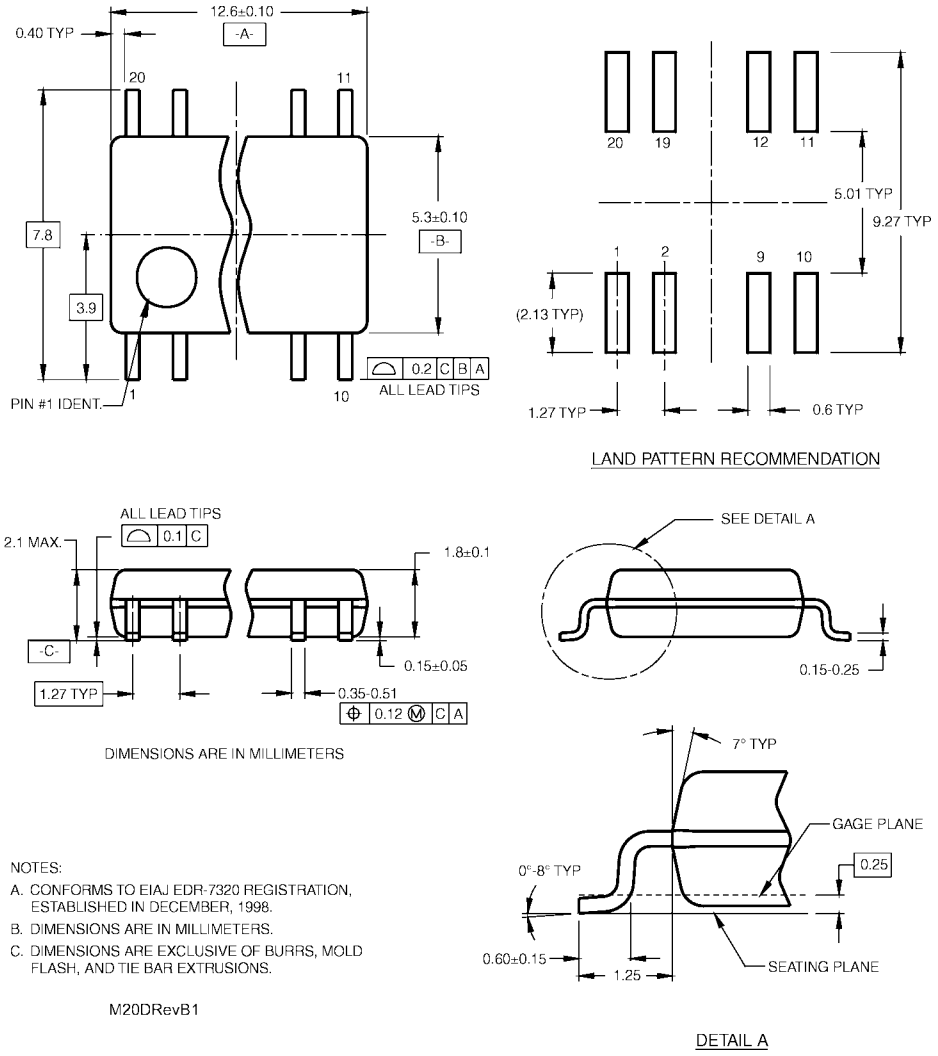
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

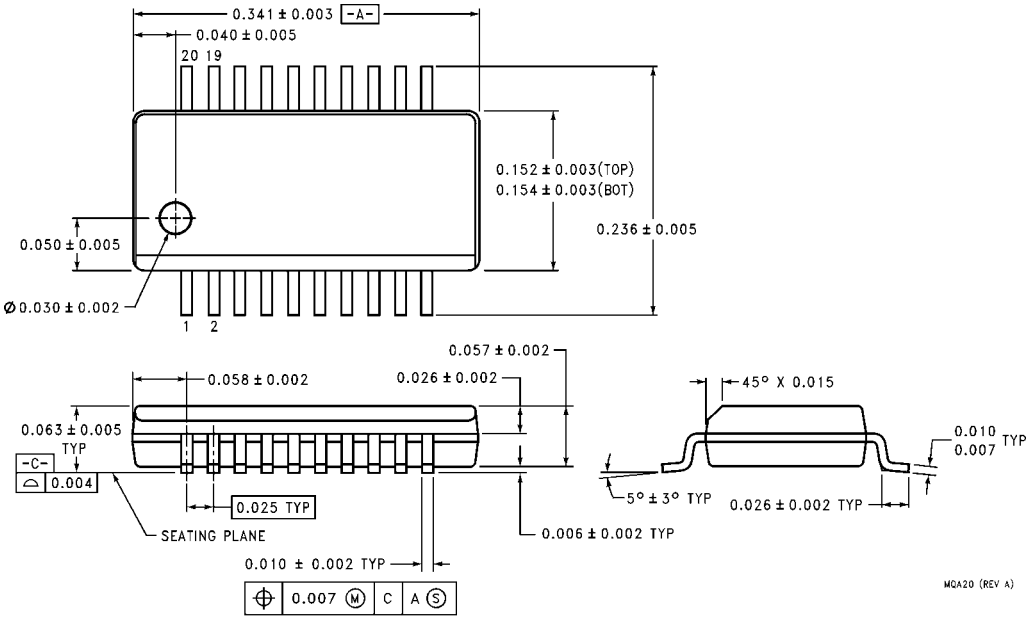
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

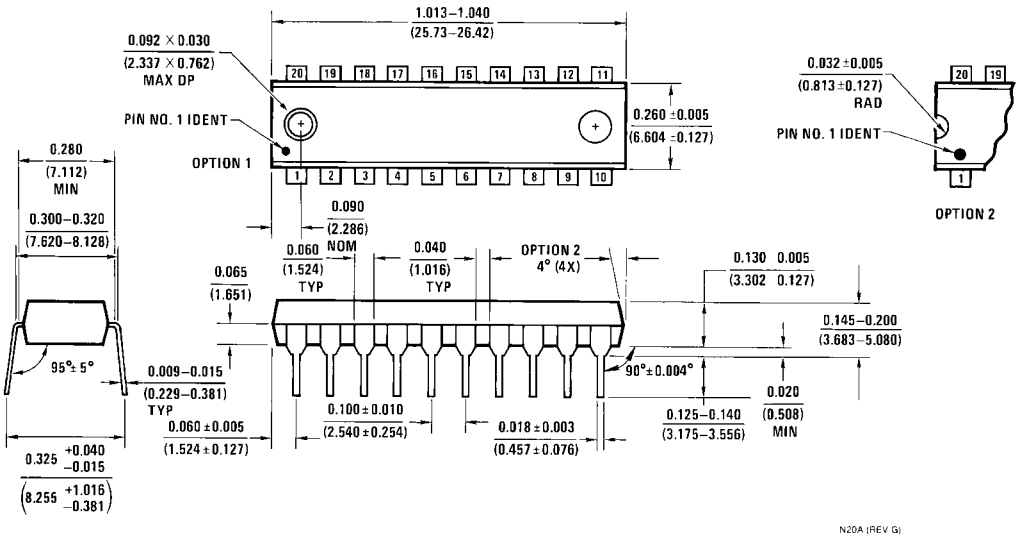
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1990
Revised September 1998

74ACQ241
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ACQ241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The ACQ utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

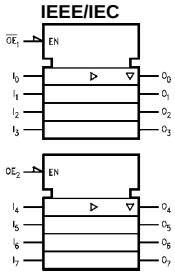
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard AC

Ordering Code:

Order Number	Package Number	Package Description
74ACQ241SC	M20B	20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300" Wide Body
74ACQ241PC	N20A	20-Lead Plastic Dual-In-Line Package, JEDEC MS-001, 0.300" Wide

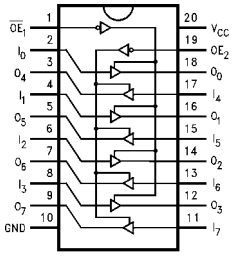
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, OE_2	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
OE_2	I_n	(Pins 3, 5, 7, 9)
H	L	L
H	H	H
H	X	Z

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	125 mV/ns
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	$I_{OUT} = -50\ \mu A$
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		3.0		2.56	2.46		$I_{OH} = -12$ mA
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 2)
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		3.0		0.36	0.44		$I_{OL} = 12$ mA
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	$V_I = V_{CC}$, GND
I_{OLD}	Minimum Dynamic Output Current	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	(Note 3)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH}
							$V_I = V_{CC}$, GND
							$V_O = V_{CC}$, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figures 1, 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figures 1, 2 (Note 5)(Note 6)
V_{IHD}	Minimum High Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. n−1 Inputs switching 0V to 5V . Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.0	6.5	9.0	2.0	9.5	ns
t_{PLH}	Data to Output	5.0	1.5	4.5	6.0	1.5	6.5	
t_{PZL}	Output Enable Time	3.3	2.5	8.0	13.0	2.5	13.5	ns
t_{PZH}		5.0	1.5	5.5	8.5	1.5	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	8.5	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	5.5	9.5	1.0	10.0	
t_{OSHL} t_{OSLH}	Output to Output Skew Data to Output (Note 9)	3.3		1.0	1.5		1.5	ns

Note 8: Voltage Range 5.0 is 5.0V ±0.5V. Voltage Range 3.3 is 3.3V ±0.3V.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the word generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope

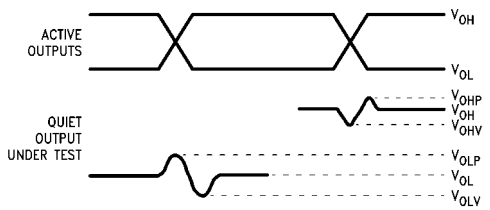


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 10: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 11: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

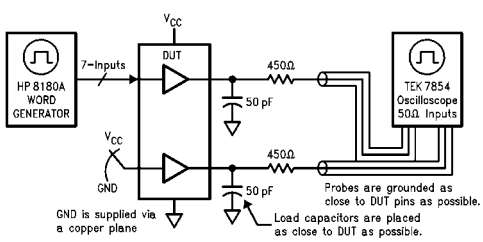
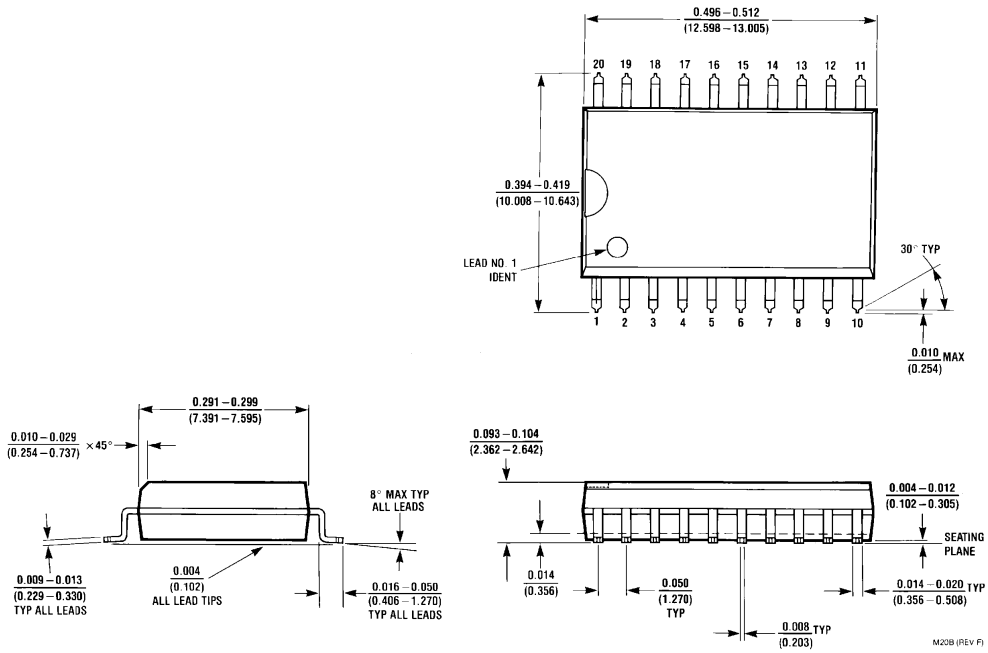


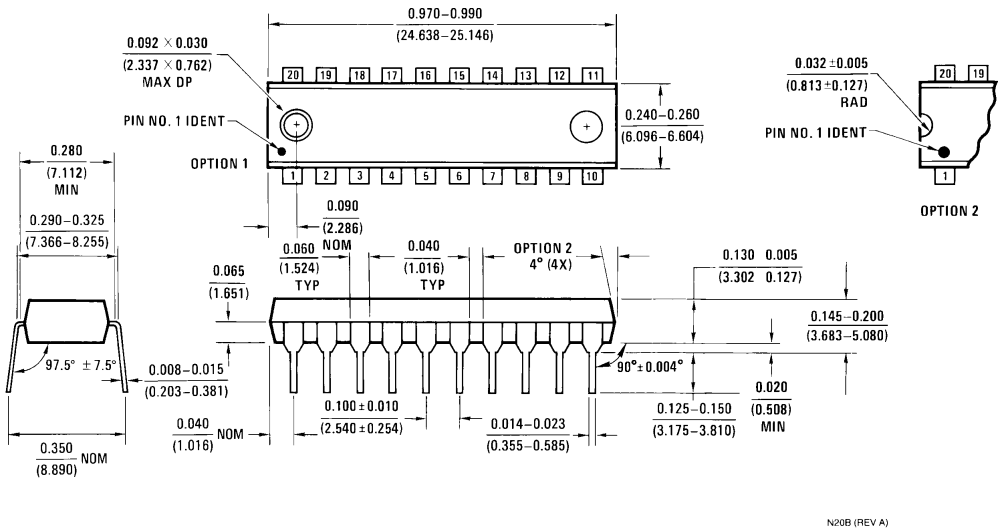
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package, JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1989
Revised November 1999

74ACQ244 • 74ACTQ244
Quiet Series™ Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The ACQ/ACTQ244 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The ACQ/ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

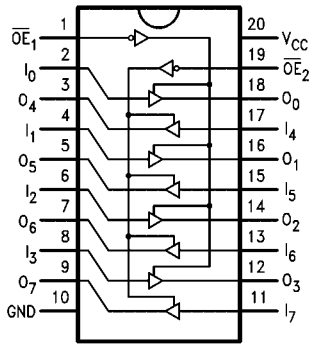
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard AC/ACT244

Ordering Code:

Order Number	Package Number	Package Description
74ACQ244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACQ244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQ244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACTQ244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ244QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74ACTQ244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

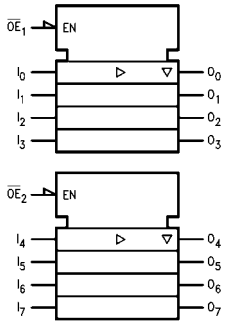


Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Logic Symbol

IEE/IEC



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	In	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	In	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Inmaterial
Z = HIGH Impedance

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I(OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n − 1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 8)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 9)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package.

DC Electrical Characteristics for ACTQ (Continued)

Note 11: Max number of outputs defined as (n). Data Inputs are driven 0V to 3V. One output @ GND.

Note 12: Max number of Data Inputs (n) switching. (n–1) Inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.0	7.0	9.0	2.0	9.5	ns
t_{PLH}	Data to Output	5.0	1.5	5.0	6.0	1.5	6.5	
t_{PZL} t_{PZH}	Output Enable Time	3.3	2.5	8.0	12.0	2.5	12.5	ns
		5.0	1.5	6.5	8.0	1.5	8.5	
t_{PHZ} t_{PLZ}	Output Disable Time	3.3	1.0	9.0	13.5	1.0	14.0	ns
		5.0	1.0	7.5	9.0	1.0	9.5	
t_{OSHL} t_{OSLH}	Output to Output	3.3		1.0	1.5		1.5	ns
	Skew Data to Output (Note 14)	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V.

Voltage Range 3.3 is 3.3V ± 0.3V.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	1.5	5.5	6.5	1.5	7.0	ns
t_{PLH}	Data to Output							
t_{PZL}	Output Enable Time	5.0	1.5	7.0	8.5	1.5	9.0	ns
t_{PZH}								
t_{PHZ}	Output Disable Time	5.0	1.0	8.0	9.5	1.0	10.0	ns
t_{PLZ}								
t_{OSHL}	Output to Output	5.0		0.5	1.0		1.0	ns
t_{OSLH}	Skew Data to Output (Note 16)							

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 16: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

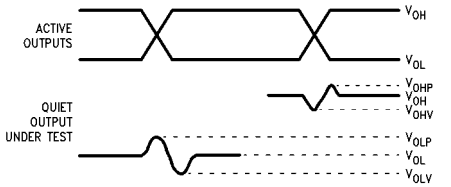
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 17: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 18: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case active and enable transition. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

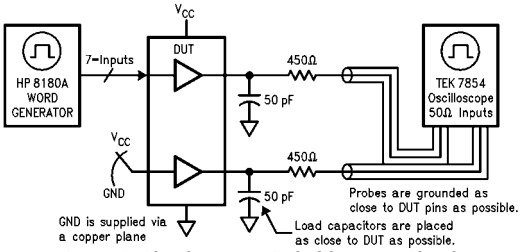
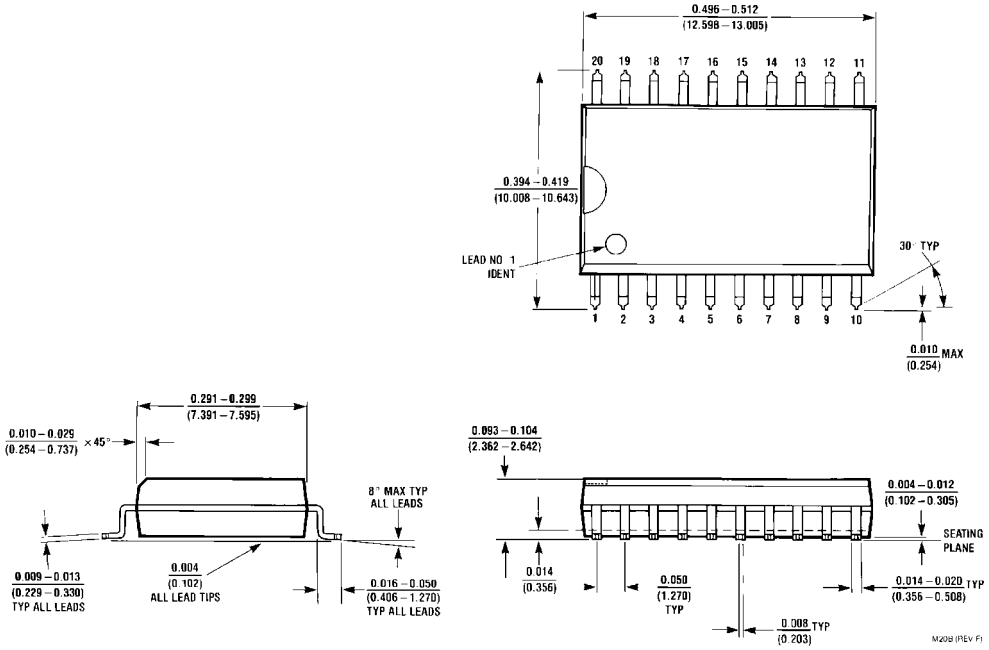


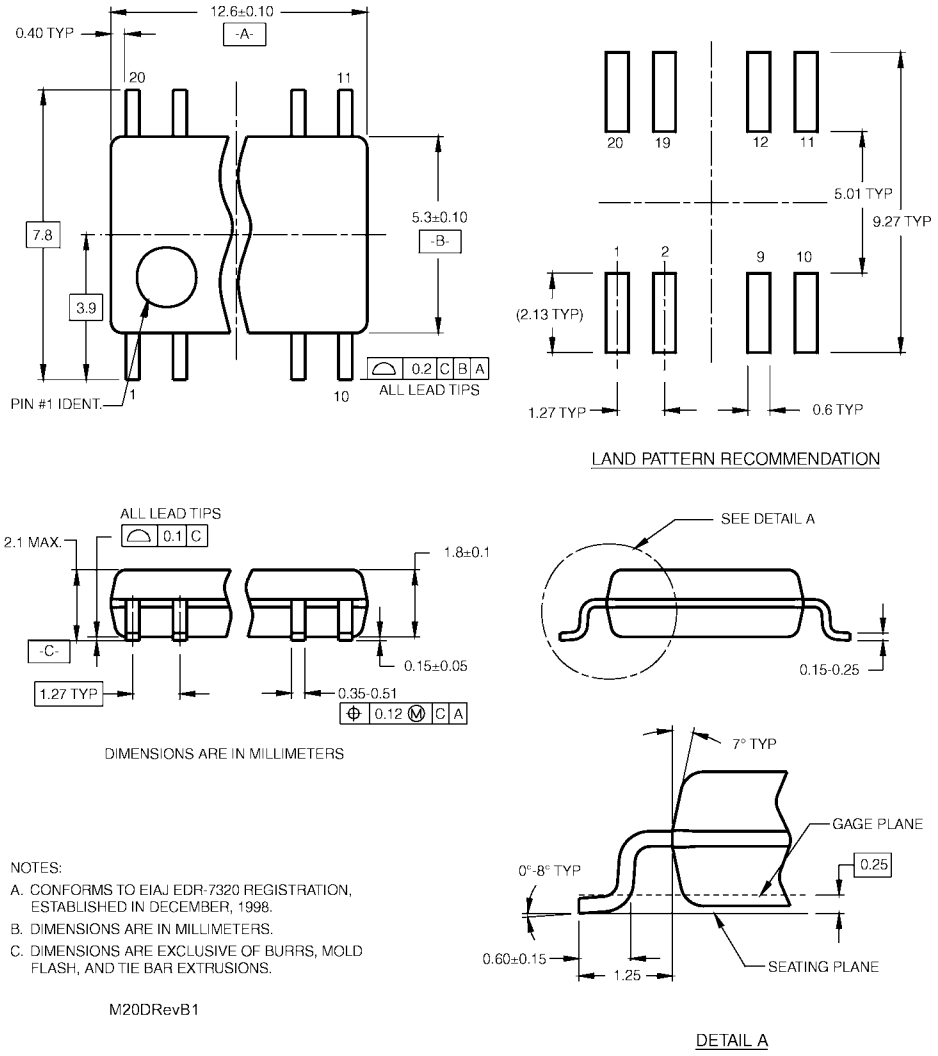
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

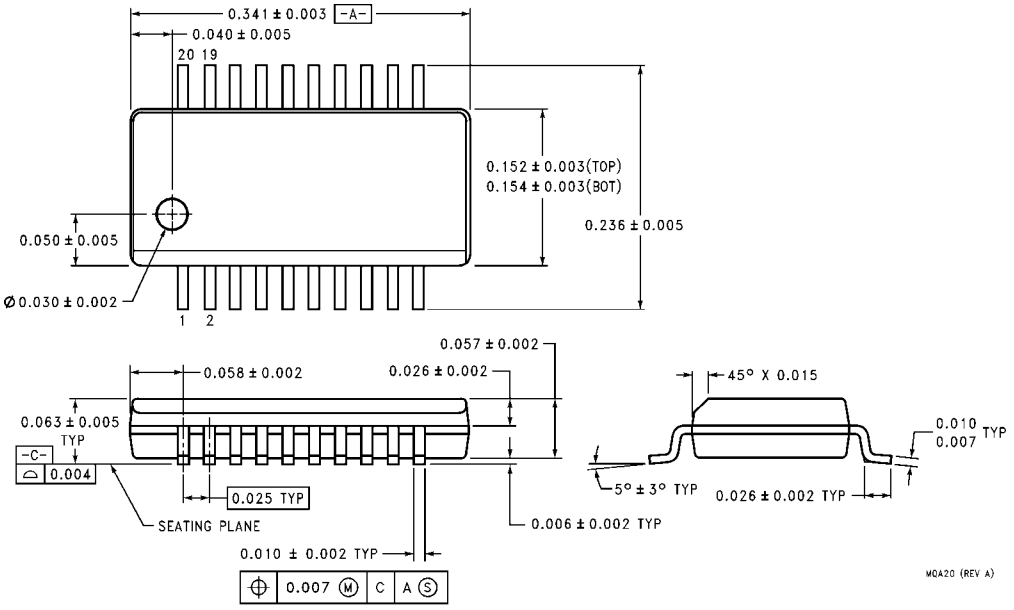
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

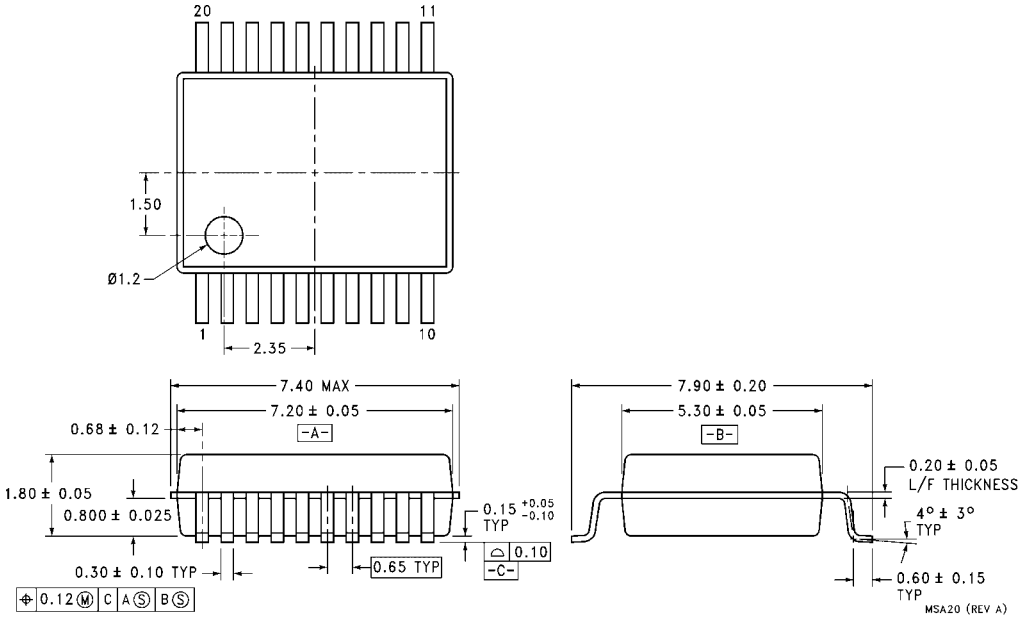
M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

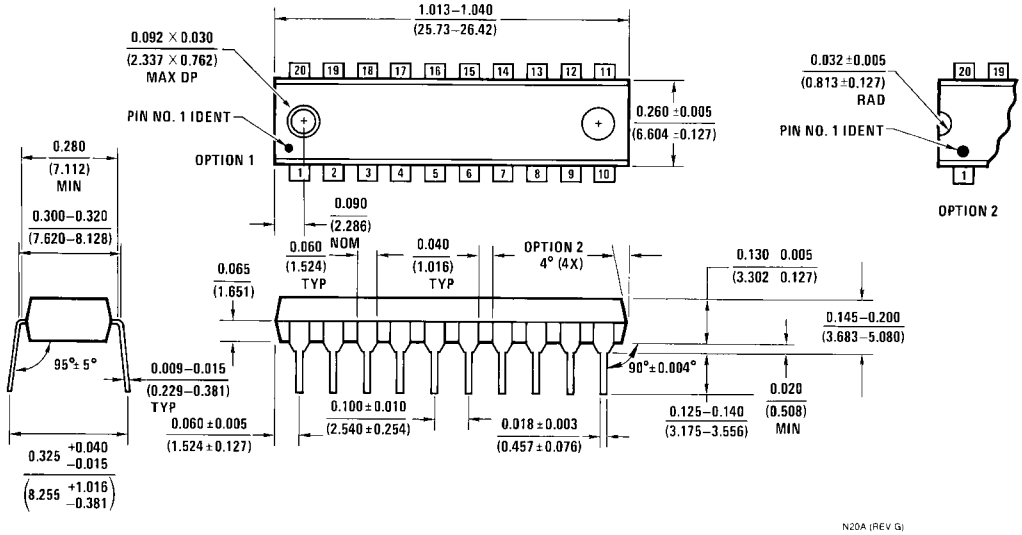


20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA20



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

July 1989
Revised November 1999

74ACQ245 • 74ACTQ245
Quiet Series™ Octal Bidirectional Transceiver with 3-STATE Inputs/Outputs

General Description

The ACQ/ACTQ245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at both the A and B ports. The Transmit/Receive (T/R) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

The ACQ/ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

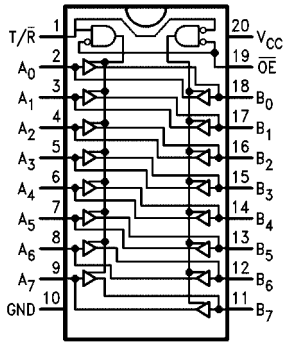
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard ACT245

Ordering Code:

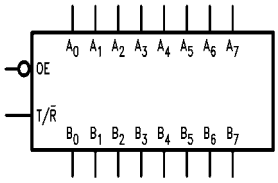
Order Number	Package Number	Package Description
74ACQ245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACQ245SJ	M20D	20-Lead Small Outline Package (SOP) EIAJ TYPE II, 5.3mm Wide
74ACQ245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACTQ245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACTQ245SJ	M20D	20-Lead Small Outline Package (SOP) EIAJ TYPE II, 5.3mm Wide
74ACTQ245QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150” Wide
74ACTQ245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACTQ245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

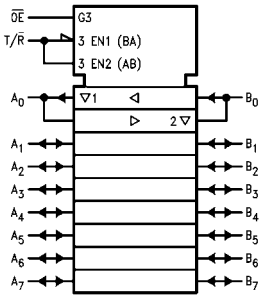
Connection Diagram



Logic Symbols



IEEE/IEC



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A 3-STATE Inputs or 3-STATE Outputs
B_0–B_7	Side B 3-STATE Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.3	±3.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V; one output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n−1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 8)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OZT}	Maximum 3-STATE Leakage Current	5.5		±0.3	±3.0	µA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 9)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package.

Note 11: Max number of outputs defined as (n). n−1 Data Inputs are driven 0V to 3V; one output @ GND.

Note 12: Max number of Data Inputs (n) switching. (n−1) Inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}) f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.0	7.5	10.0	2.0	10.5	ns
t_{PLH}	Data to Output	5.0	1.5	5.0	6.5	1.5	7.0	
t_{PZL}	Output Enable Time	3.3	3.0	8.5	13.0	3.0	13.5	ns
t_{PZH}		5.0	2.0	6.0	8.5	2.0	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	8.5	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	7.5	9.5	1.0	10.0	
t_{OSHL}	Output to Output Skew (Note 14)	3.3		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	1.5	5.5	7.0	1.5	7.5	ns
t_{PLH}	Data to Output							
t_{PZL}, t_{PZH}	Output Enable Time	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PHZ}, t_{PLZ}	Output Disable Time	5.0	1.0	8.0	10.0	1.0	10.5	ns
t_{OSHL}	Output to Output Skew (Note 16)	5.0		0.5	1.0		1.0	ns
t_{OSLH}	Data to Output							

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Note 16: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
$C_{I/O}$	Input/Output Capacitance	15	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	80.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

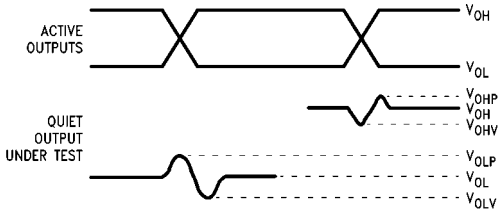


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 17: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 18: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

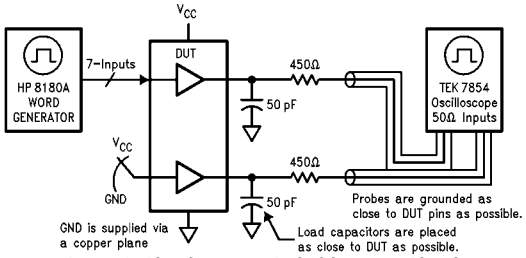
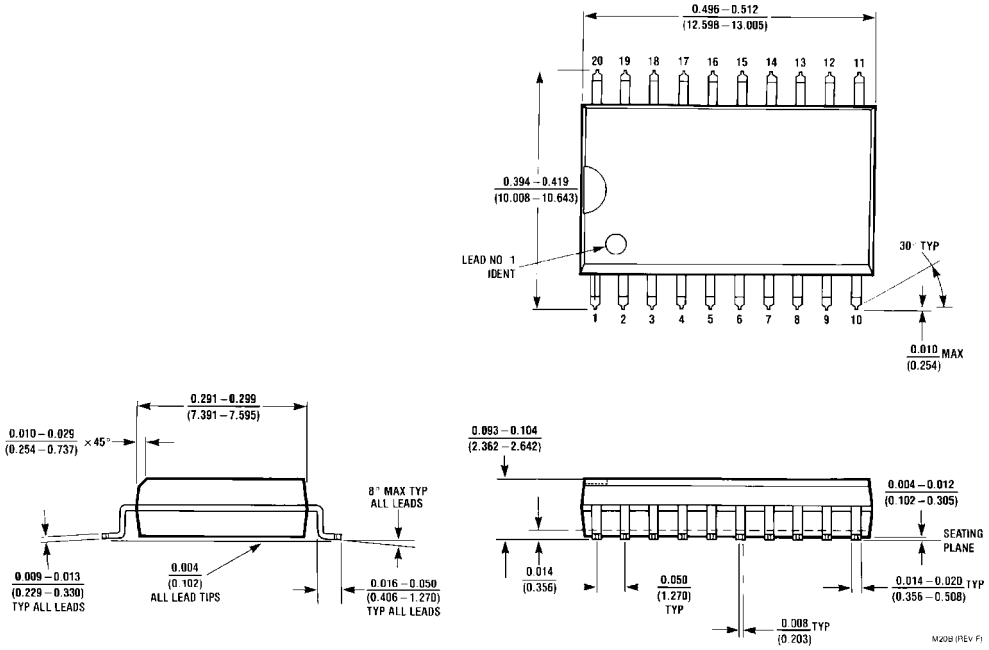


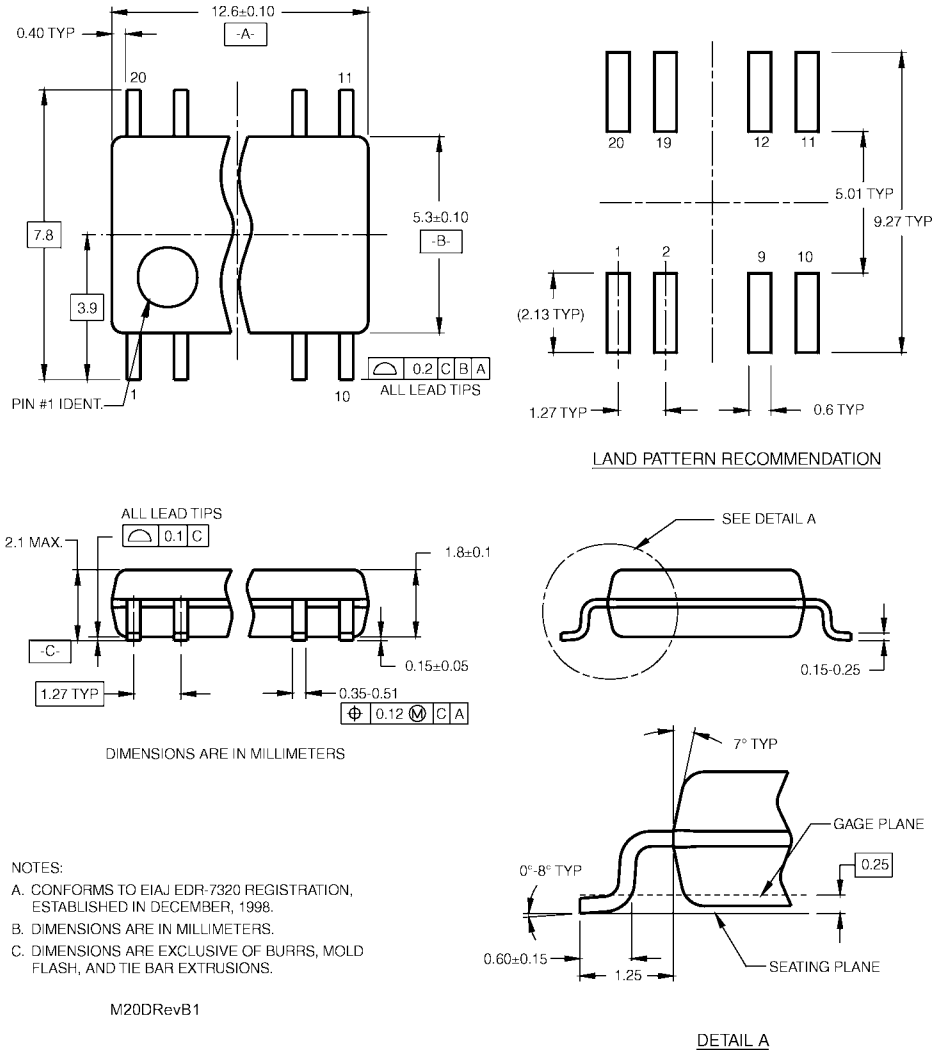
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

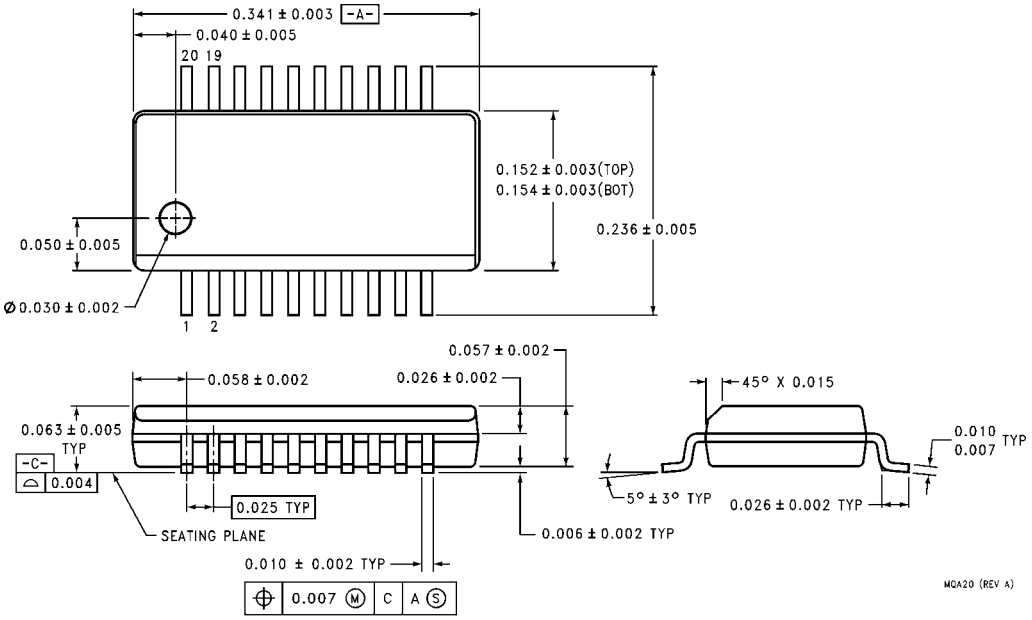
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

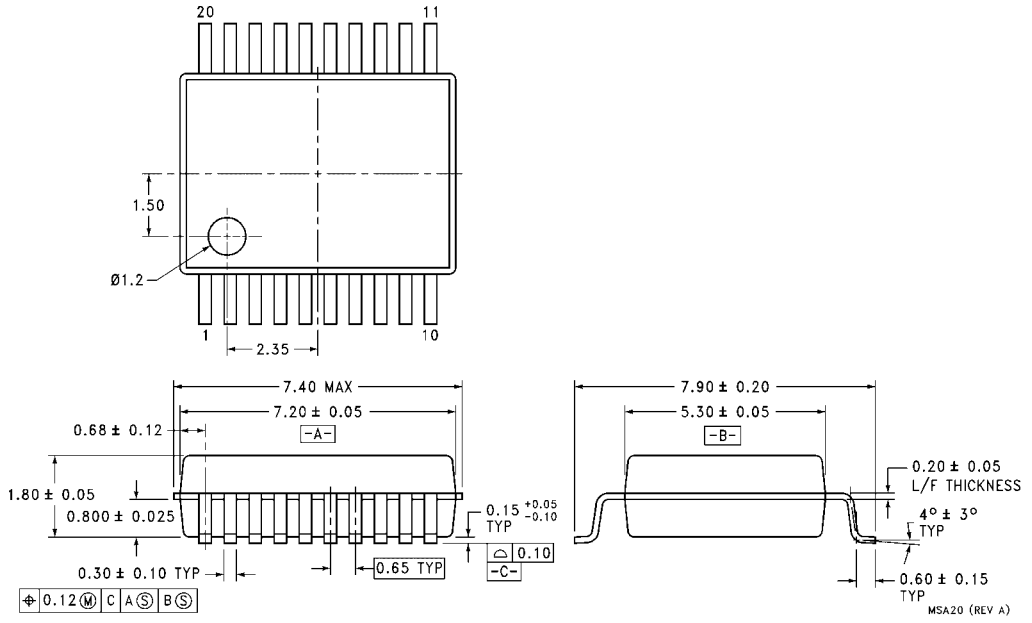
M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

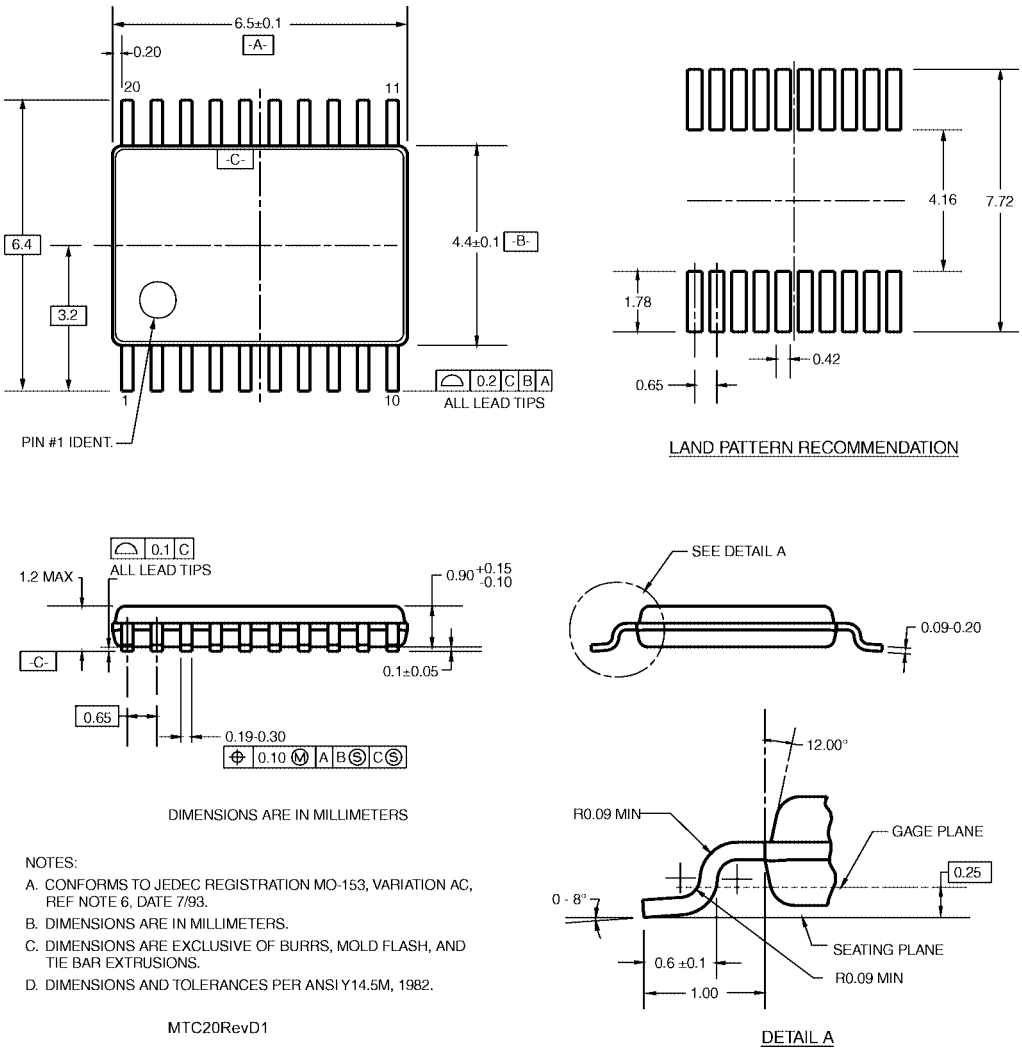


20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA20



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

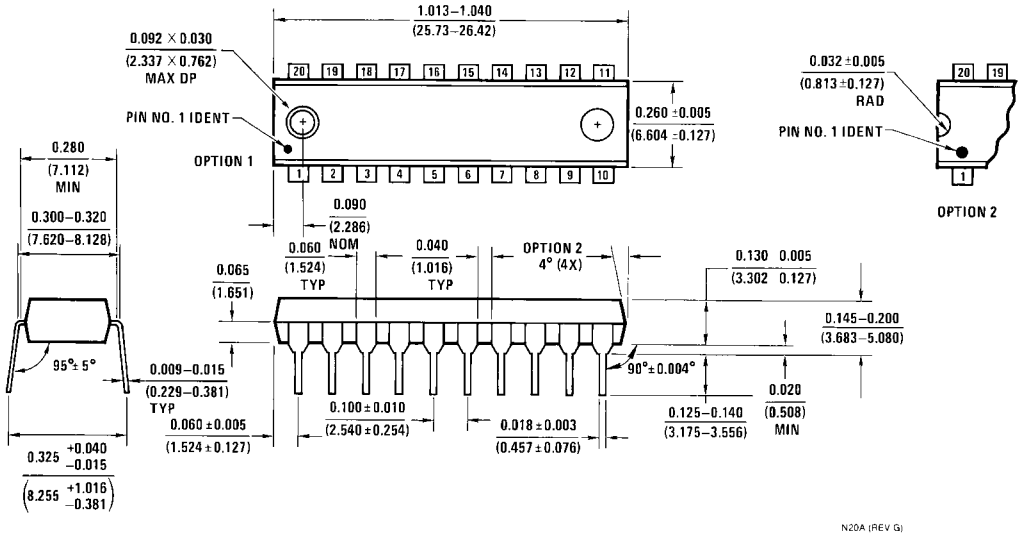
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1989
Revised November 1999

74ACQ373 • 74ACTQ373 Quiet Series™ Octal Transparent Latch with 3-STATE Outputs

General Description

The ACQ/ACTQ373 consists of eight latches with 3-STATE outputs for bus organized system applications. The latches appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the bus output is in the HIGH impedance state.

The ACQ/ACTQ373 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

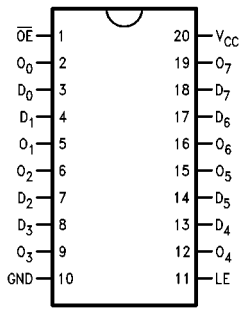
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch up immunity
- Eight latches in a single package
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard AC/ACT373

Ordering Code:

Order Number	Package Number	Package Description
74ACQ373SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACQ373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQ373PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001m 0.300" Wide
74ACTQ373SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQT373QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74ACTQ373PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001m 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

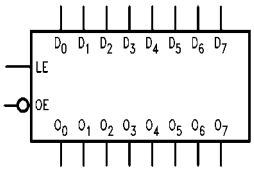


Pin Descriptions

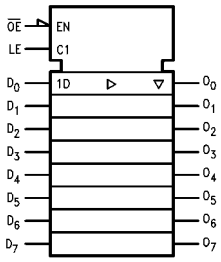
Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

FACT™, Quiet Series™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC



Functional Description

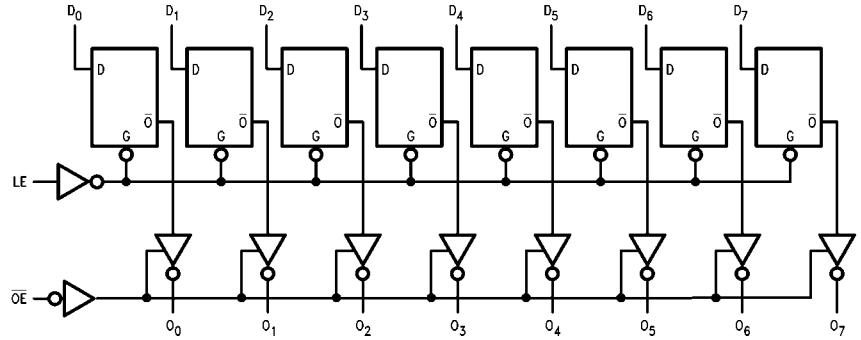
The ACQ/ACTQ373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latchup Source	
or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
V_{OLP}	Quiet Output	5.0	1.1	1.5		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)
V_{OLV}	Quiet Output	5.0	−0.6	−1.2		V	Figure 2, Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of data inputs (n) switching. (n–1) inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 8)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 9)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC}, or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: Plastic DIP package.

Note 11: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 12: Max number of data inputs (n) switching. (n–1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.5	8.0	10.5	2.5	11.0	ns
t_{PLH}	D_n to O_n	5.0	1.5	5.5	7.0	1.5	7.5	
t_{PHL}	Propagation Delay	3.3	2.5	8.0	12.0	2.5	12.5	ns
t_{PLH}	LE to O_n	5.0	2.0	6.0	8.0	2.0	8.5	
t_{PZL}	Output Enable Time	3.3	2.5	8.5	13.0	2.5	13.5	ns
t_{PZH}		5.0	1.5	6.5	8.5	1.5	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	9.0	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	6.5	9.5	1.0	10.0	
t_{OSHL}	Output to Output Skew	3.3		1.0	1.5		1.5	ns
t_{OSLH}	D_n to O_n(Note 14)	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V.

Voltage Range 3.3 is 3.3V ± 0.3V.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	0	3.0	3.0	ns
	D_n to LE	5.0	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	0	1.5	1.5	ns
	D_n to LE	5.0	0	1.5	1.5	
t_W	LE Pulse Width, HIGH	3.3	2.0	4.0	4.0	ns
		5.0	2.0	4.0	4.0	

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V.

Voltage Range 3.3 is 3.3V ± 0.3V.

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	2.0	6.5	7.5	2.0	8.0	ns
t_{PLH}	D_n to O_n							
t_{PHL}	Propagation Delay	5.0	2.5	7.0	8.5	2.5	9.0	ns
t_{PLH}	LE to O_n							
t_{PZL}	Output Enable	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PZH}	Time							
t_{PHZ}	Output Disable	5.0	1.0	8.0	10.0	1.0	10.5	ns
t_{PLZ}	Time							
t_{OSHL}	Output to Output Skew	5.0		0.5	1.0		1.0	ns
t_{OSLH}	D_n to O_n(Note 17)							

Note 16: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 18)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0	1.5	1.5	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	4.0	4.0	ns

Note 18: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	44.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

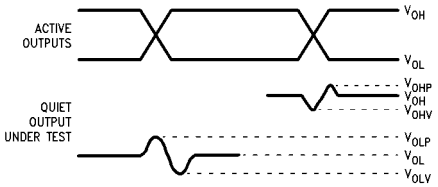
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note A: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note B: Input pulses have the following characteristics:

f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH} until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

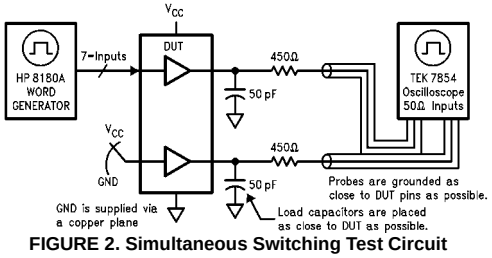
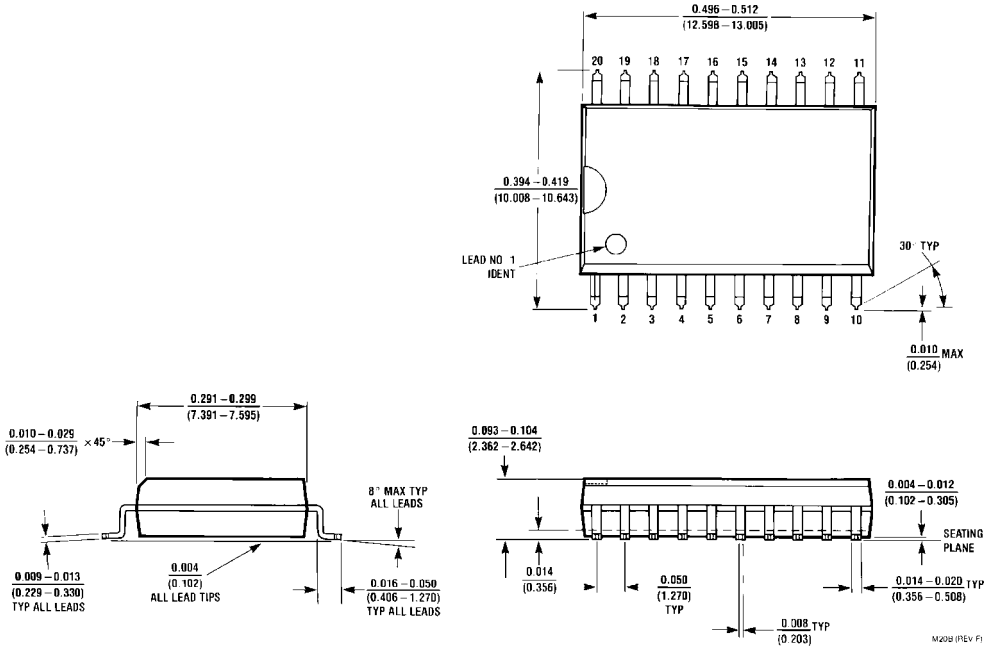


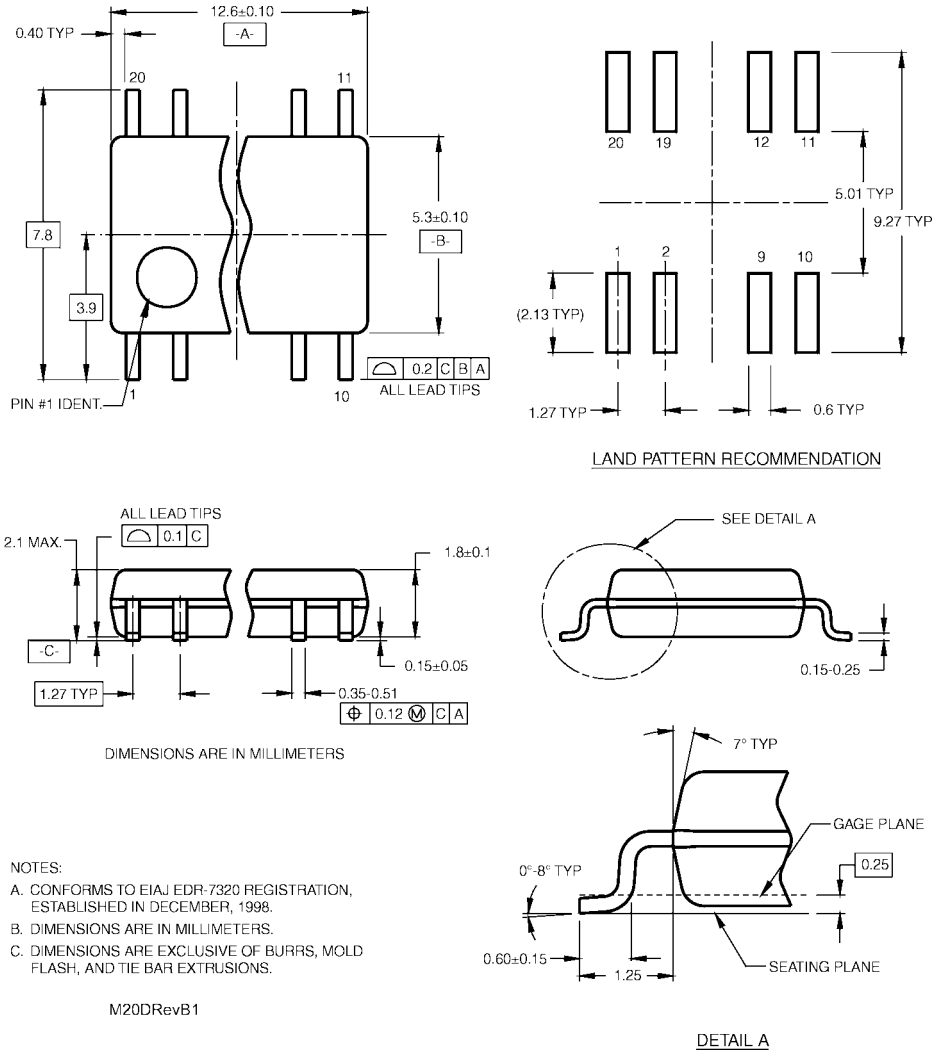
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

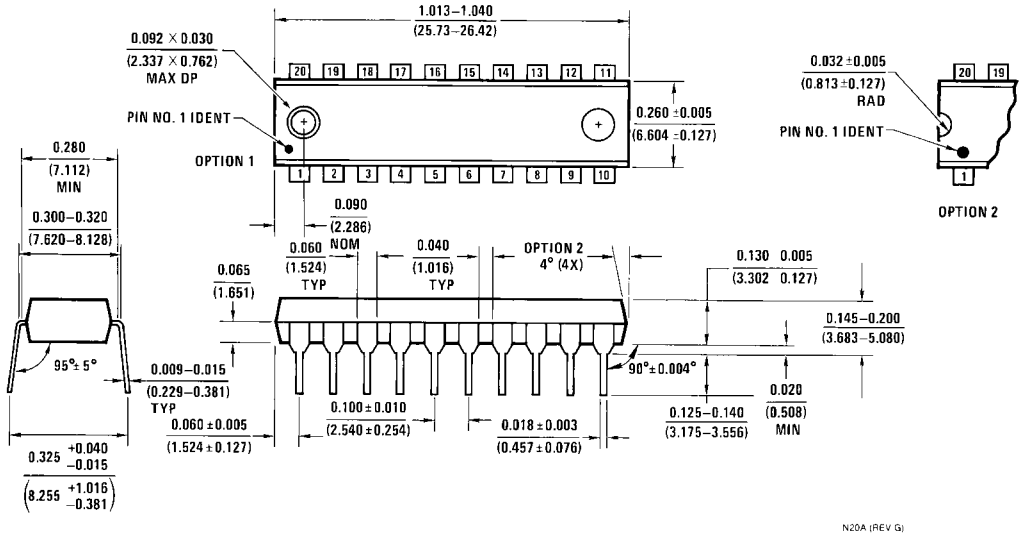
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1989
Revised November 1999

74ACQ374 • 74ACTQ374
Quiet Series™ Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACQ/ACTQ374 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

The ACQ/ACTQ374 utilizes FACT Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

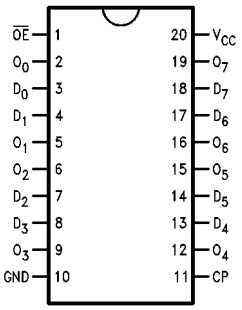
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- Buffered positive edge-triggered clock
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard AC/ACT374

Ordering Code:

Order Number	Package Number	Package Description
74ACQ374SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACQ374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQ374PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACTQ374SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ374QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74ACTQ374PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

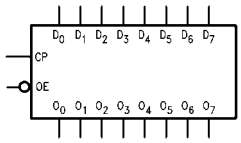


Pin Descriptions

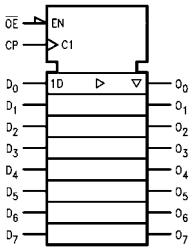
Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

FACT™, Quiet Series™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC



Functional Description

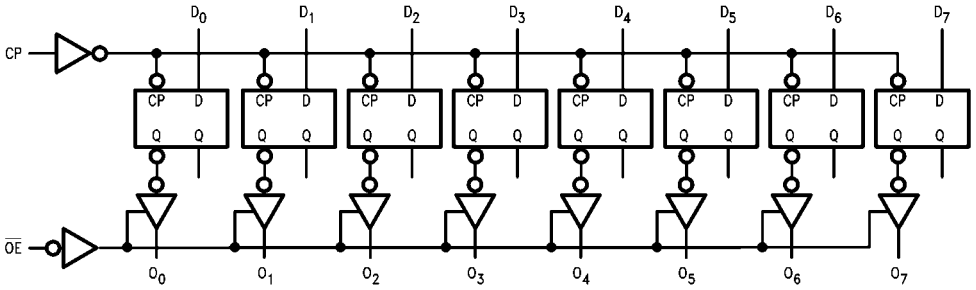
The ACQ/ACTQ374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
V_{OLP}	Quiet Output	5.0	1.1	1.5		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP Package.

Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of data inputs (n) switching. (n−1) inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 µA
		4.5 5.5		3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 µA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 8)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	µA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input (Note 4)	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 8)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package.

Note 11: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND

Note 12: Max number of data inputs (n) switching. (n−1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	3.3	75			70		MHz
		5.0	90			85		
t_{PLH} t_{PHL}	Propagation Delay CP to O_n	3.3	3.0	9.5	13.0	3.0	13.5	ns
		5.0	2.0	6.5	8.5	2.0	9.0	
t_{PZL} t_{PZH}	Output Enable Time	3.3	3.0	9.5	13.0	3.0	13.5	ns
		5.0	2.0	6.5	8.5	2.0	9.0	
t_{PHZ} t_{PLZ}	Output Disable Time	3.3	1.0	9.5	14.5	1.0	15.0	ns
		5.0	1.0	8.0	9.5	1.0	10.0	
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 14) CP to O_n	3.3		1.0	1.5		1.5	ns
		5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	3.3	0	3.0	3.0	ns
		5.0	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW D_n to CP	3.3	0	1.5	1.5	ns
		5.0	2.0	1.5	1.5	
t_W	CP Pulse Width, HIGH or LOW	3.3	2.0	4.0	4.0	ns
		5.0	2.0	4.0	4.0	

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	85			80		MHz
t_{PLH} t_{PHL}	Propagation Delay CP to O_n	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PZL} t_{PZH}	Output Enable Time	5.0	2.0	7.5	9.0	2.0	9.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time	5.0	1.0	8.0	10.0	1.0	10.5	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 17) CP to O_n	5.0		0.5	1.0		1.0	ns

Note 16: Voltage Range 5.0 is 5.0V ± 0.5V

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 18)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	1.5	1.5	ns
t_H	CP Pulse Width, HIGH or LOW	5.0	2.0	4.0	4.0	ns

Note 18: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	42.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

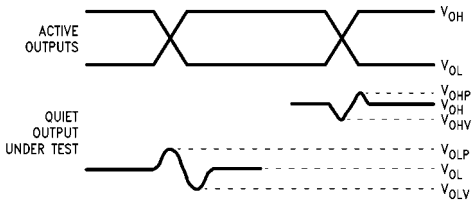
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 19: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 20: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

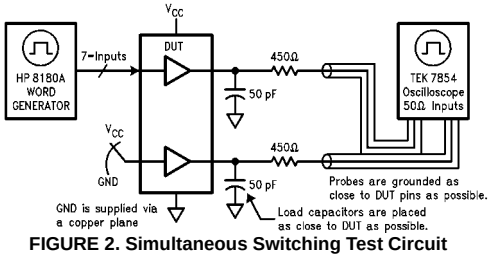
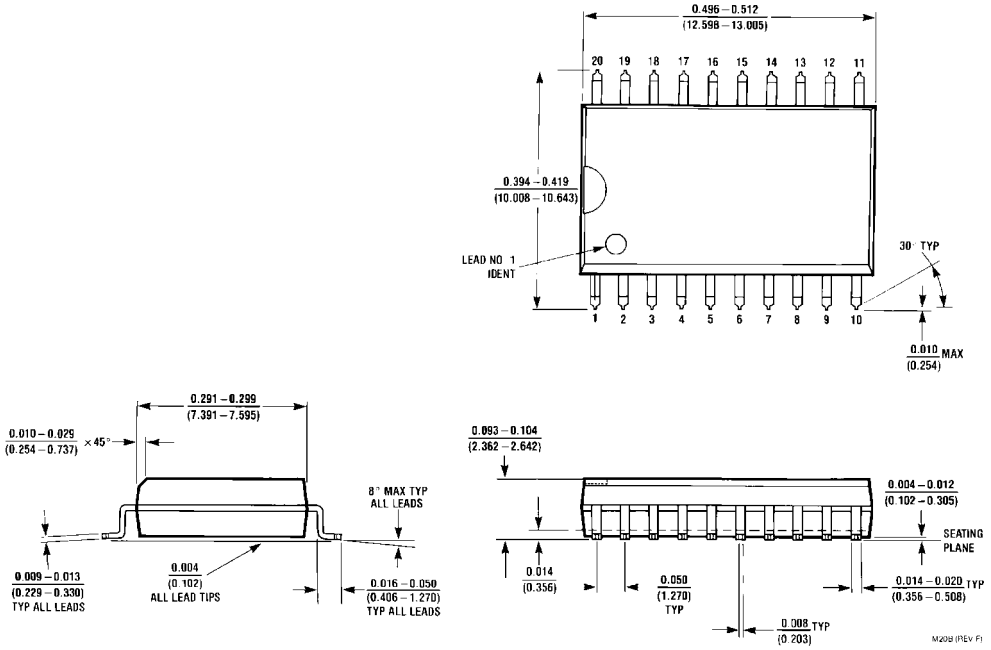


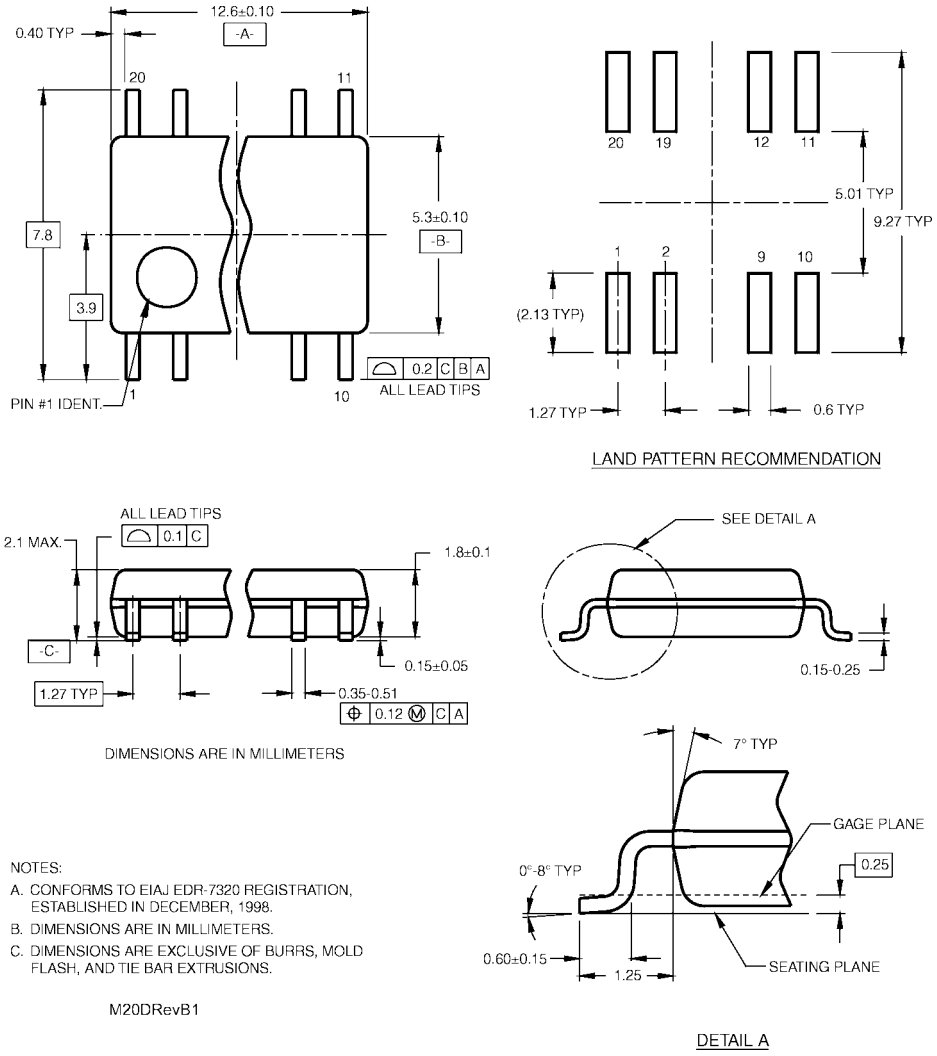
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

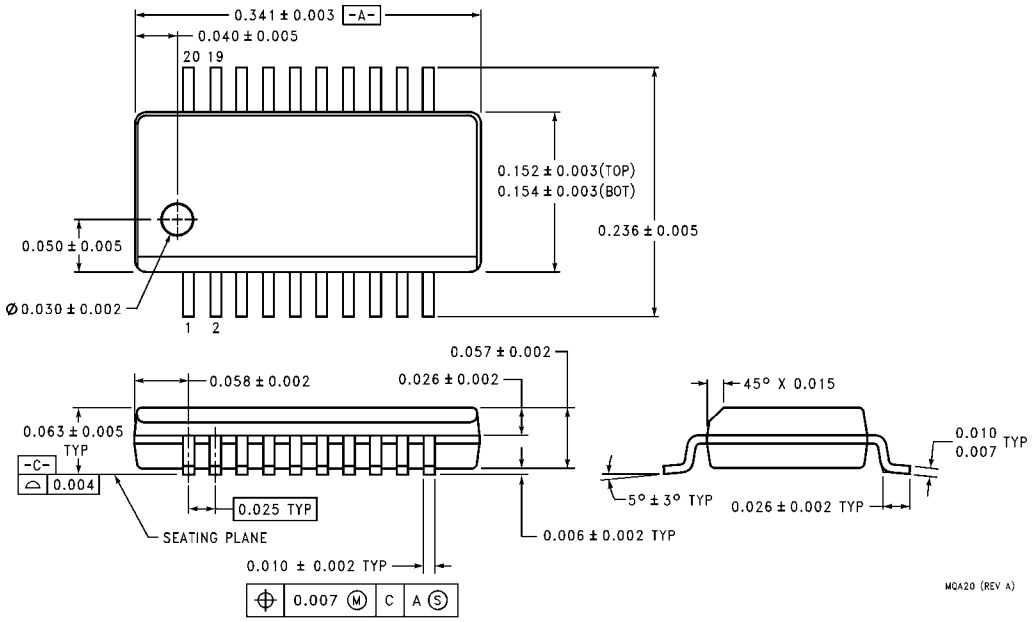
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

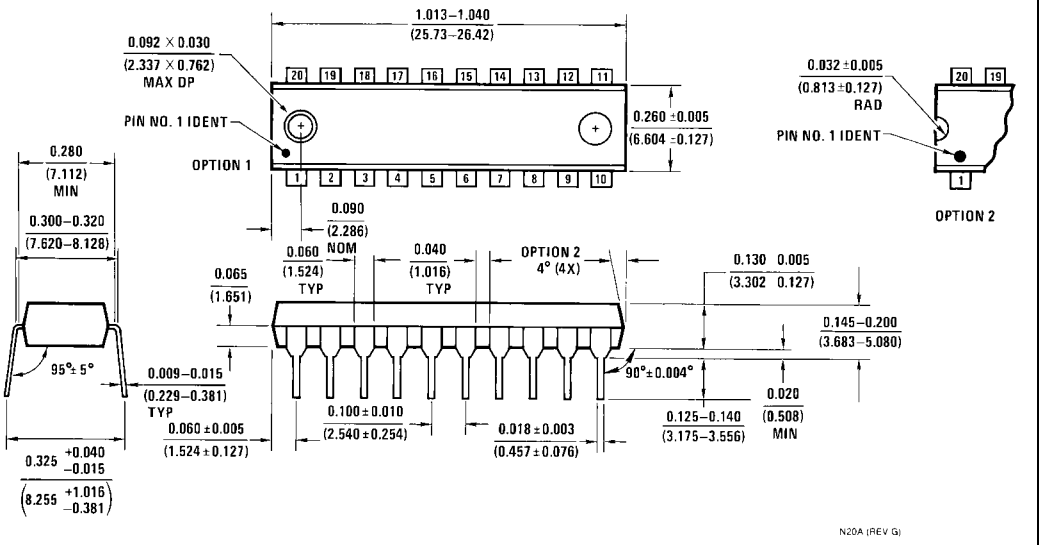
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1990
Revised November 1998

74ACQ543• 74ACTQ543
Quiet Series™ Octal Registered Transceiver with 3-STATE Outputs

General Description

The ACQ/ACTQ543 is a non-inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The ACQ/ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- 8-bit octal latched transceiver
- Separate controls for data flow in each direction
- Back-to-back registers for storage
- Outputs source/sink 24 mA
- 300 mil slim PDIP/SOIC

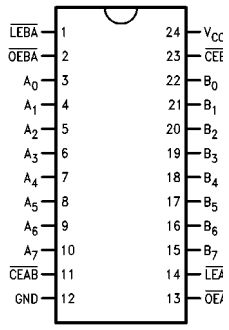
Ordering Code:

Order Number	Package Number	Package Description
74ACQ543SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACQ543SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
74ACTQ543SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ543QSC	MQA24	24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-1.7, 0.150" Wide
74ACTQ543SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the order code.

Connection Diagram

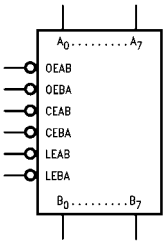
Pin Assignment for DIP, SOIC and QSOP



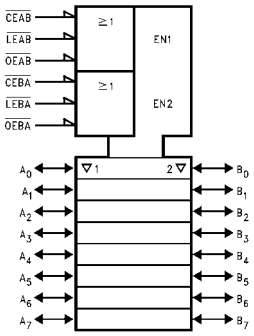
Pin Descriptions

Pin Names	Description
$\overline{OEAB}$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}$	B-to-A Latch Enable Input (Active LOW)
A_0–A_7	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B_0–B_7	B-to-A Data Inputs or A-to-B 3-STATE Outputs

Logic Symbols



IEEE/IEC



Functional Description

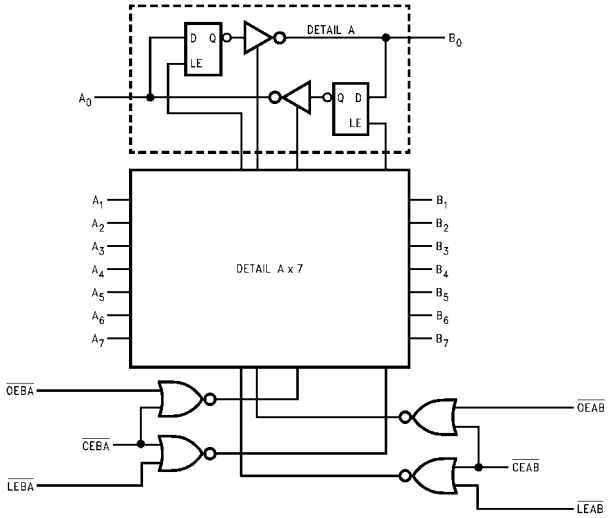
The ACQ/ACTQ543 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from A_0–A_7 or take data from B_0–B_7, as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$ inputs

Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source or	
Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage V_{CC}	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		I_{OUT} = −50 μA
	Output Voltage	4.5	4.49	4.4	4.4	V	
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		I_{OUT} = 50 μA
	Output Voltage	4.5	0.001	0.1	0.1	V	
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		± 0.6	± 6.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	–0.6	–1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: Plastic DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n–1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
		5.5	1.5	2.0	2.0		or V_{CC} – 0.1V
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
		5.5	1.5	0.8	0.8		or V_{CC} – 0.1V
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = –50 µA
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = –24 mA
		5.5		4.86	4.76		I_{OH} = –24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 8)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	$V_I = V_{CC}$, GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.6	6.0	µA	$V_{(OE)} = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ – 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 9)	5.5			–75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	–0.6	–1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package

Note 11: Max number of outputs defined as (n). (n–1) Data Inputs are driven 0V to 3V, one output @ GND.

Note 12: Max number of Data Inputs (n) switching. (n–1) Inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f =1 MHz.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	8.0	11.0	1.5	11.5	
t_{PHL}	Transparent Mode	5.0	1.5	5.0	7.0	1.5	7.5	ns
	A_n to B_n or B_n to A_n							
t_{PLH}	Propagation Delay	3.3	1.5	9.0	12.5	1.5	13.0	ns
t_{PHL}	$\overline{LEBA}$, $\overline{LEAB}$ to A_n, B_n	5.0	1.5	6.0	8.0	1.5	8.5	
t_{PZH}	Output Enable Time							
t_{PZL}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	3.3	1.5	10.5	15.0	1.5	15.5	ns
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	5.0	1.5	7.0	9.5	1.5	10.0	
t_{PHZ}	Output Disable Time							
t_{PLZ}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	3.3	1.0	8.0	11.0	1.0	11.5	ns
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	5.0	1.0	5.0	7.0	1.0	7.5	
t_{OSHL}	Output to Output	3.3		1.0	1.5		1.5	ns
t_{OSLH}	Skew (Note 14)	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ±0.5V

Voltage Range 3.3 is 3.3V ±0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for AC

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3		3.0	3.0	ns
	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0				
t_H	Hold Time, HIGH or LOW	3.3		1.5	1.5	ns
	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0				
t_W	Latch Enable	3.3		4.0	4.0	ns
	Pulse Width, LOW	5.0				

Note 15: Voltage Range 5.0 is 5.0V ±0.5V

Voltage Range 3.3 is 3.0V ±0.3V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay Transparent Mode A_n to B_n or B_n to A_n	5.0	1.5	5.5	7.5	1.5	8.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEBA}$, $\overline{LEAB}$ to A_n, B_n	5.0	1.5	6.5	8.5	1.5	9.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n $\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	5.0	1.5	8.0	10.0	1.5	10.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n $\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	5.0	1.0	5.5	7.5	1.0	8.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 17)	5.0		0.5	1.0		1.0	ns

Note 16: Voltage Range 5.0 is 5.0V ±0.5V

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 18)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0		3.0	3.0	ns
t_S	Hold Time, HIGH or LOW A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0		1.5	1.5	ns
t_W	Latch Enable Pulse Width, LOW	5.0		4.0	4.0	ns

Note 18: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

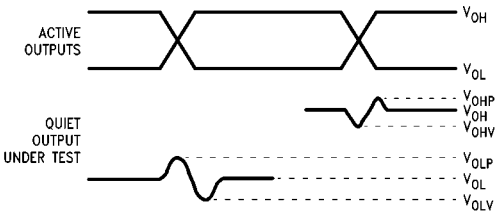


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 19: $V_{OHV}$and V_{OLP} are measured with respect to ground reference.

Note 20: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability on the measurements.

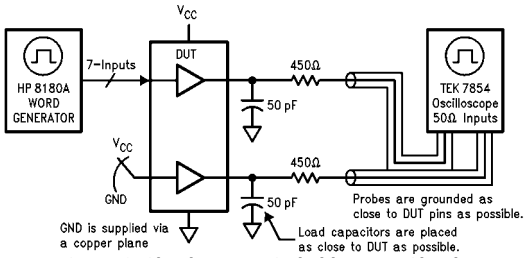
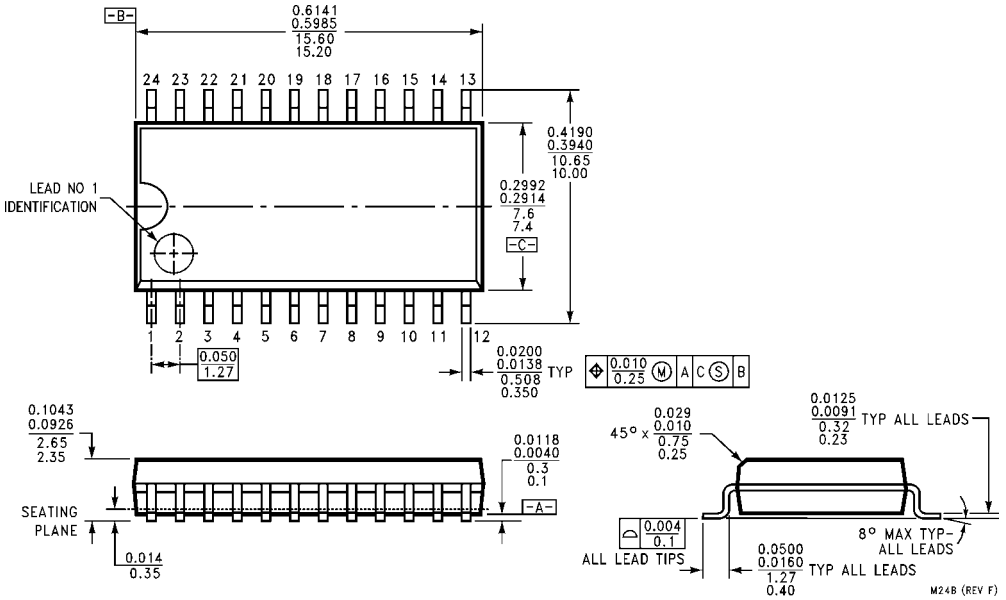
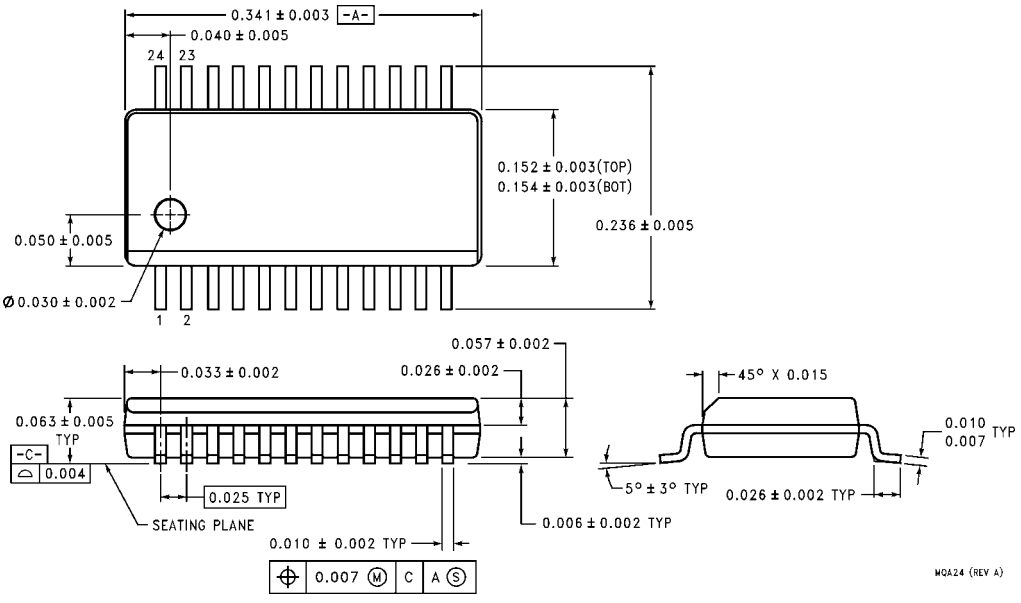


FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted

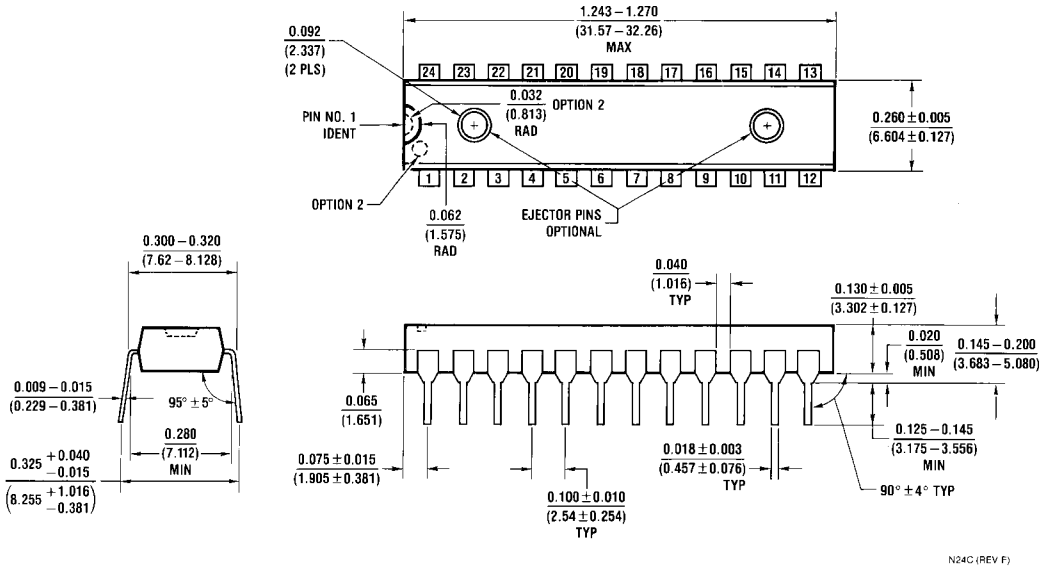


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B



24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-1.7, 0.150" Wide
Package Number MQA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1990
Revised December 1998

74ACQ544 • 74ACTQ544
Quiet Series™ Octal Registered Transceiver with 3-STATE Outputs

General Description

The ACQ/ACTQ544 is an inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow. The 544 inverts data in both directions.

The ACQ/ACTQ utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- 8-bit inverting octal latched transceiver
- Separate controls for data flow in each direction
- Back-to-back registers for storage
- Outputs source/sink 24 mA

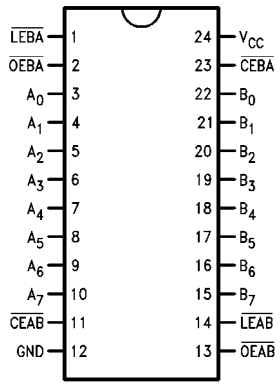
Ordering Code:

Order Number	Package Number	Package Description
74ACQ544SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACQ544SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
74ACTQ544SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ544SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for DIP and SOIC

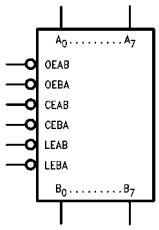


Pin Descriptions

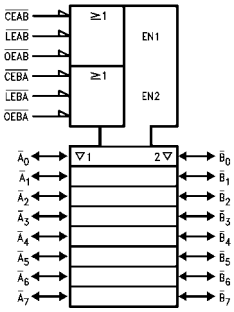
Pin Names	Description
$\overline{OEAB}$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}$	B-to-A Latch Enable Input (Active LOW)
$\overline{A_0}$ –$\overline{A_7}$	A-to-B Data Inputs or B-to-A 3-STATE Outputs
$\overline{B_0}$ –$\overline{B_7}$	B-to-A Data Inputs or A-to-B 3-STATE Outputs

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC



Functional Description

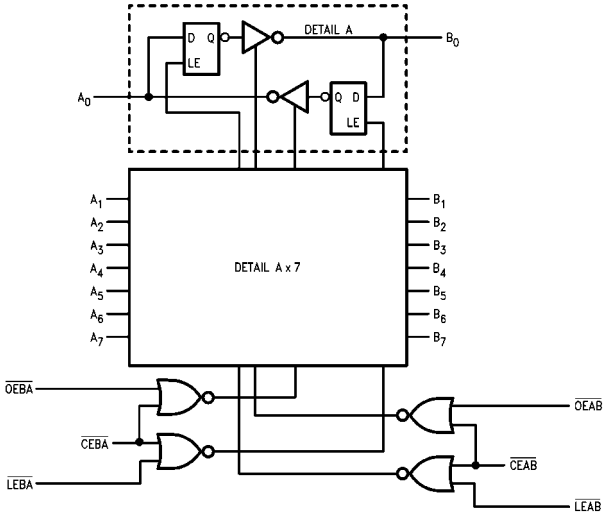
The ACQ/ACTQ544 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from $\overline{A_0}$ –$\overline{A_7}$ or take data from $\overline{B_0}$ –$\overline{B_7}$, as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$ inputs.

Data I/O Control Table

Inputs			Latch	Output
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$	Status	Buffers
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source or	
Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage V_{CC}	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		I_{OUT} = − 50 μA
	Output Voltage	4.5	4.49	4.4	4.4	V	
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = − 12 mA
		4.5		3.86	3.76	V	I_{OH} = − 24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		I_{OUT} = 50 μA
	Output Voltage	4.5	0.001	0.1	0.1	V	
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN}= V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.6	±6.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n-1) inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). f.= 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 8)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	$V_I = V_{CC}$, GND
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.6	±6.0	µA	V_I, (OE) = V_{IL}, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic Output Current (Note 9)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}		5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent or GND	5.5		8.0	80.0	µA	$V_{IN} = V_{CC}$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Maximum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package.

Note 11: Max number of outputs defined as (n-1). Data Inputs are driven 0V to 3V, one output @ GND.

DC Electrical Characteristics for ACTQ (Continued)

Note 12: Max number of Data Inputs (n) switching (n-1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	1.5	8.0	11.0	1.5	12.0	
t_{PHL}	Transparent Mode	5.0	1.5	5.0	7.5	1.5	8.0	ns
	A_n to B_n or B_n to A_n							
t_{PLH}	Propagation Delay	3.3	1.5	8.5	12.0	1.5	12.5	ns
t_{PHL}	$\overline{LEBA}$, $\overline{LEAB}$ to A_n, B_n	5.0	1.5	6.0	8.0	1.5	8.5	
	Output Enable Time	3.3	1.5	10.0	14.0	1.5	15.0	
t_{PZH}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	5.0	1.5	7.0	9.5	1.5	10.0	ns
t_{PZL}	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n							
	Output Disable Time	3.3	1.0	7.5	10.5	1.0	11.0	
t_{PHZ}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	5.0	1.0	5.0	7.0	1.0	7.5	ns
t_{PLZ}	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n							
t_{OSHL}	Output to Output	3.3		1.0	1.5		1.5	ns
t_{OSLH}	Skew (Note 14)	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for ACQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3		3.0	3.0	ns
	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0				
t_H	Hold Time, HIGH or LOW	3.3		1.5	1.5	ns
	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0				
t_W	Latch Enable, B to A	3.3		4.0	4.0	ns
	Pulse Width, LOW	5.0				

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.0V ± 0.3V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay Transparent Mode A_n to B_n or B_n to A_n	5.0	1.5	5.5	7.5	1.5	8.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEBA}$, $\overline{LEAB}$ to A_n, B_n	5.0	1.5	6.5	8.5	1.5	9.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n $\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	5.0	1.5	8.0	10.0	1.5	10.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n $\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	5.0	1.0	5.5	7.5	1.0	8.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 17)	5.0		0.5	1.0		1.0	ns

Note 16: Voltage Range 5.0 is 5.0V ± 0.5V

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 18)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	5.0		1.5	1.5	ns
t_W	Latch Enable, B to A Pulse Width, LOW	5.0		4.0	4.0	ns

Note 18: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	80.0	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

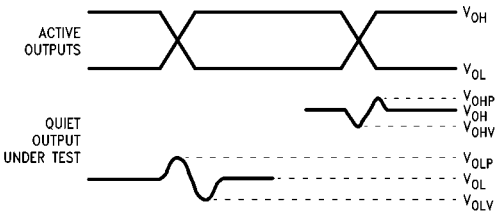
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note A. V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note B. input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability on the measurements.

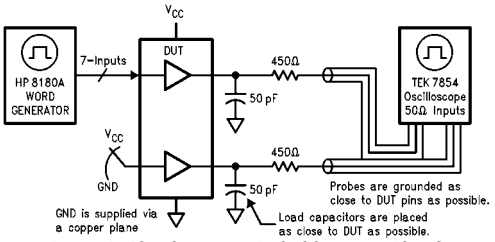
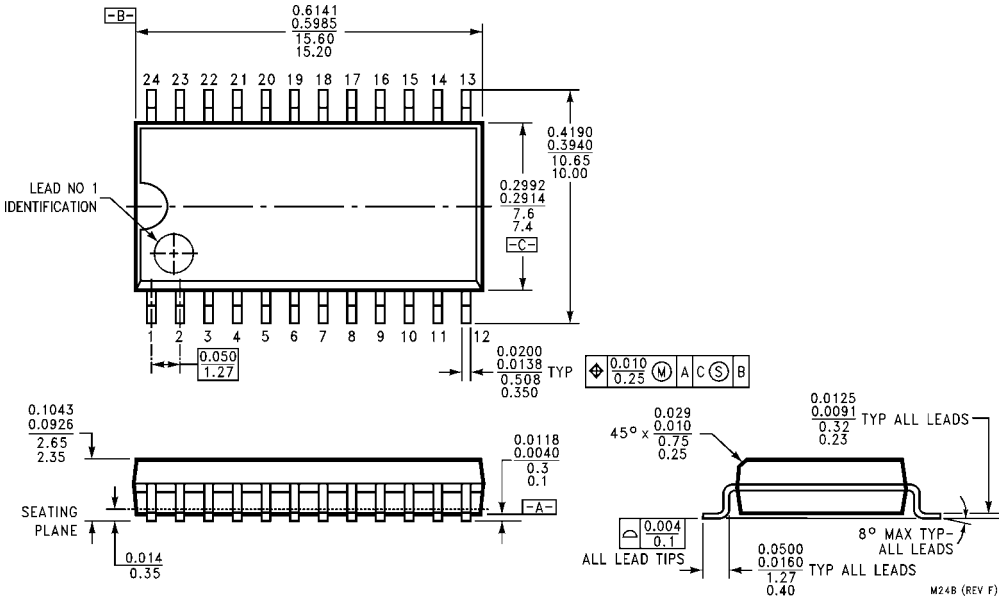


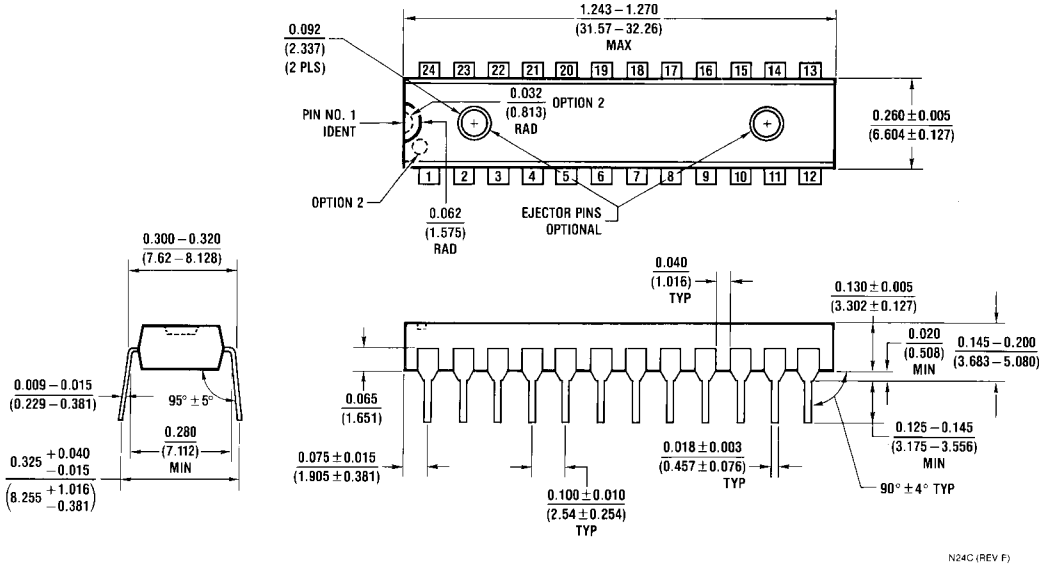
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1990
Revised November 1999

74ACQ573 • 74ACTQ573
Quiet Series™ Octal Latch with 3-STATE Outputs

General Description

The ACQ/ACTQ573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs. The ACQ/ACTQ573 is functionally identical to the ACQ/ACTQ373 but with inputs and outputs on opposite sides of the package. The ACQ/ACTQ utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

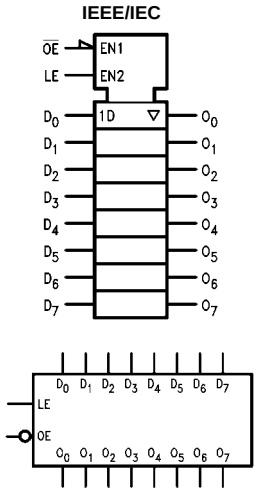
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Outputs source/sink 24 mA

Ordering Code:

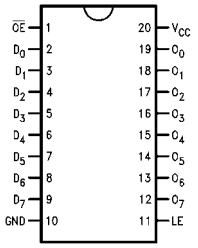
Order Number	Package Number	Package Description
74ACQ573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACQ573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQ573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACQ573PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACTQ573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ573QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74ACTQ573PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Latch Outputs

FACT™, Quiet Series™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation

Functional Description

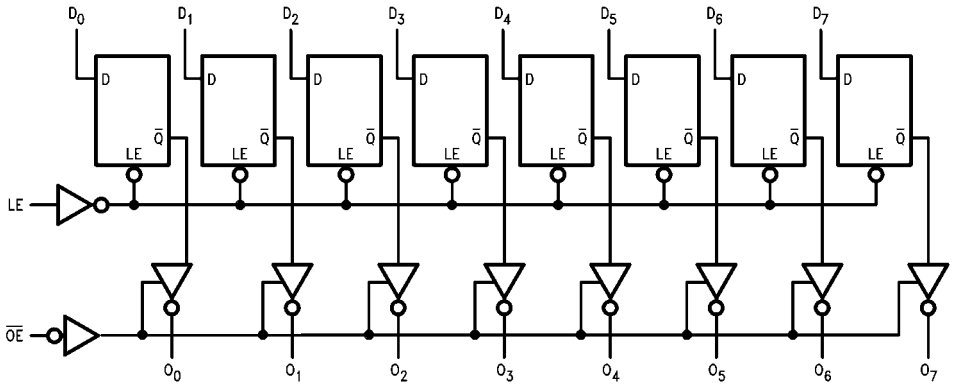
The ACQ/ACTQ573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW the latches store the information that was present on the D-type inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage
L = LOW Voltage
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latchup Source	
or Sink Current	±300 mA
Junction Temperature (T_J	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65 V_{Max}
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85 V_{Min}
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE						V_I (OE) = V_{IL}, V_{IH}
	Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{CC}, GND
							V_O = V_{CC}, GND
V_{OLP}	Quiet Output	5.0	1.1	1.5		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: Plastic DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n − 1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 8)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 9)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: Plastic DIP package.

Note 11: Max number of outputs defined as (n). Data Inputs are driven 0V to 3V. One output @ GND.

Note 12: Max number of data inputs (n) switching. (n − 1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f =1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.5	8.5	10.5	2.5	11.0	ns
t_{PLH}	D_n to O_n	5.0	1.5	5.5	7.0	1.5	7.5	
t_{PLH}	Propagation Delay	3.3	2.5	8.5	12.0	2.5	12.5	ns
t_{PHL}	LE to O_n	5.0	2.0	6.0	8.0	2.0	8.5	
t_{PZL}	Output Enable Time	3.3	2.5	8.5	13.0	2.5	13.5	ns
t_{PZH}		5.0	1.5	6.0	8.5	1.5	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	9.0	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	6.0	9.5	1.0	10.0	
t_{OSHL}	Output to Output Skew (Note 14)	3.3		1.0	1.5		1.5	ns
t_{OSLH}	D_n to O_n	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	0	3.0	3.0	ns
	D_n to LE	5.0	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	0	1.5	1.5	ns
	D_n to LE	5.0	0	1.5	1.5	
t_W	LE Pulse Width, HIGH	3.3	2.0	4.0	4.0	ns
		5.0	2.0	4.0	4.0	

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	2.0	6.5	7.5	2.0	8.0	ns
t_{PLH}	$D_n$to O_n							
t_{PLH}	Propagation Delay	5.0	2.5	7.0	8.5	2.5	9.0	ns
t_{PHL}	LE to O_n							
t_{PZL}, t_{PZH}	Output Enable Time	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PHZ}, t_{PLZ}	Output Disable Time	5.0	1.0	8.0	10.0	1.0	10.5	ns
t_{OSHL}	Output to Output Skew (Note 17)	5.0		0.5	1.0		1.0	ns
t_{OSLH}	D_n to O_n							

Note 16: Voltage Range 5.0 is 5.0V ± 0.5V

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 18)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0	1.5	1.5	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	4.0	4.0	ns

Note 18: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	42.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

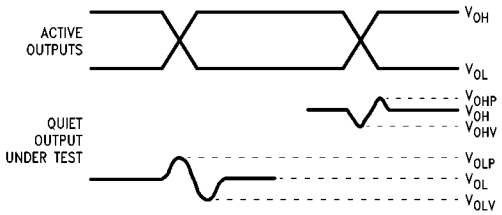
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 19: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 20: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

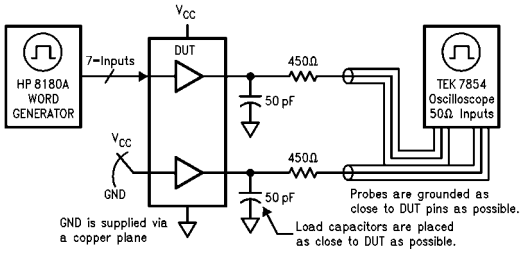
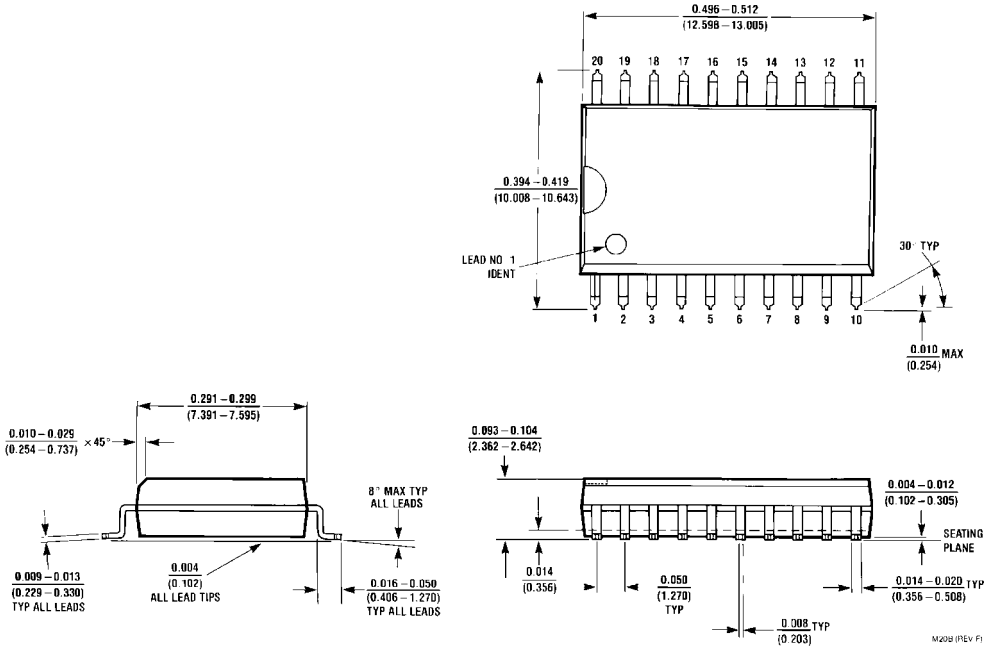


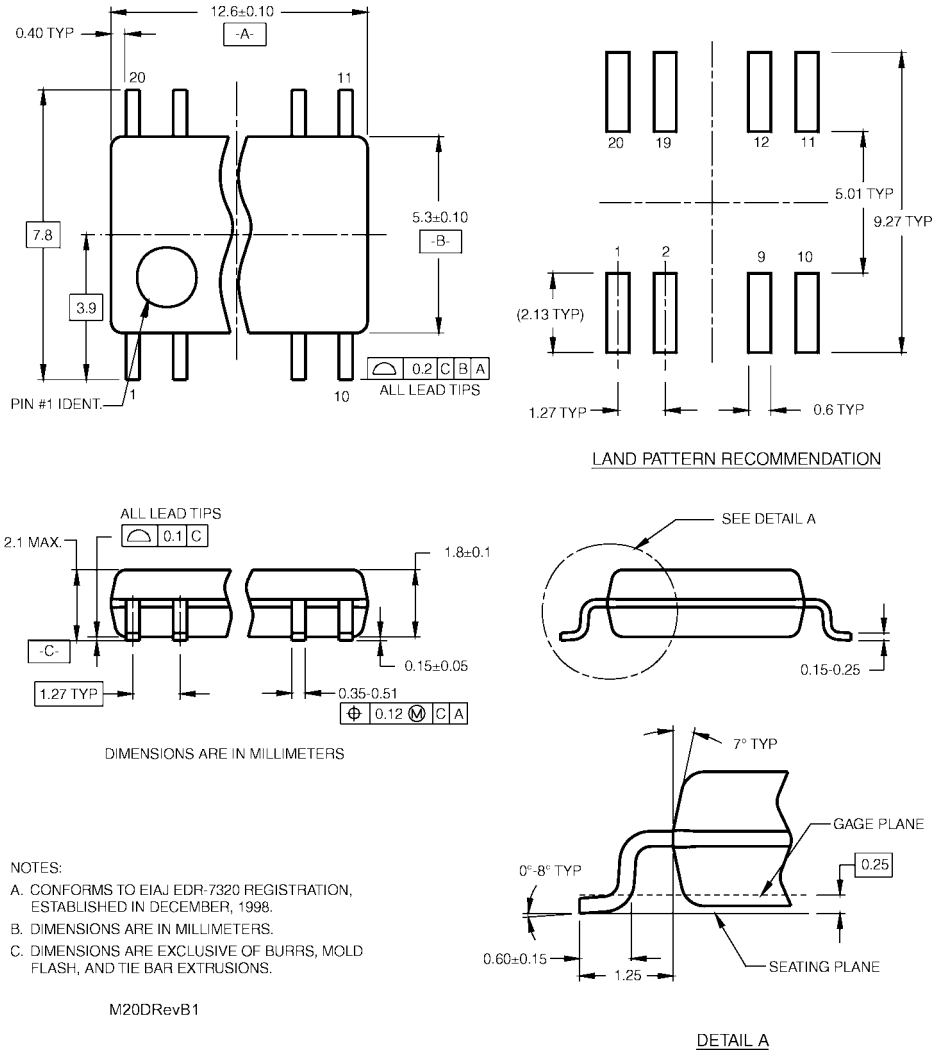
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

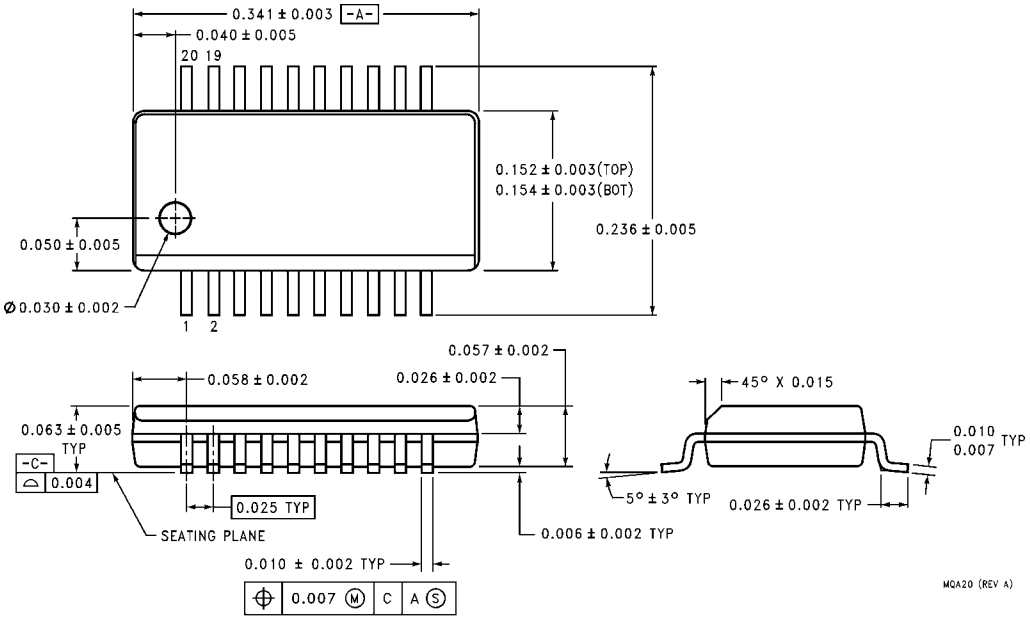
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

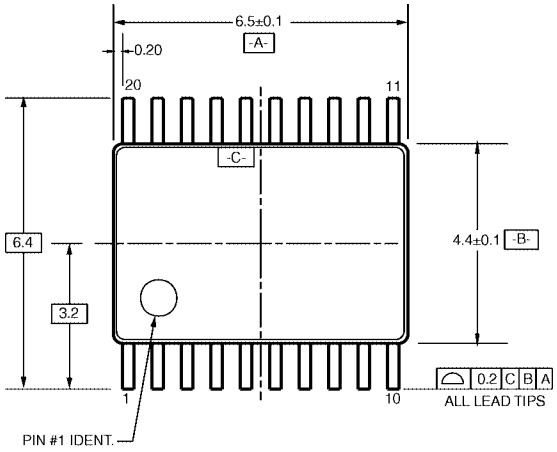
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

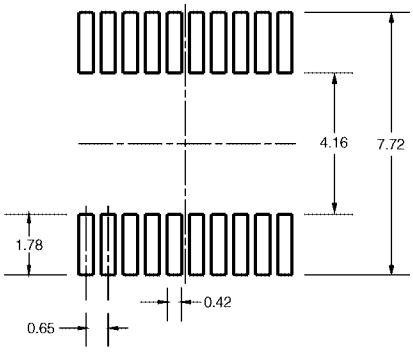
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



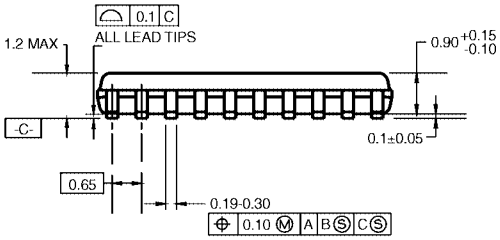
20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA20

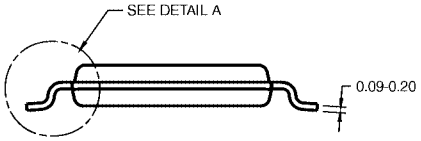
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

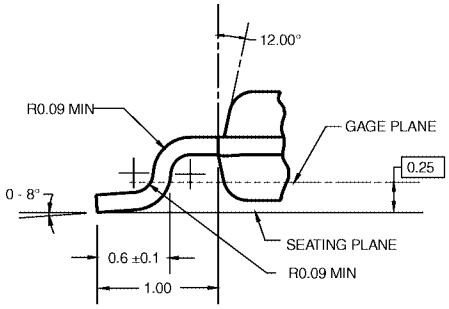
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

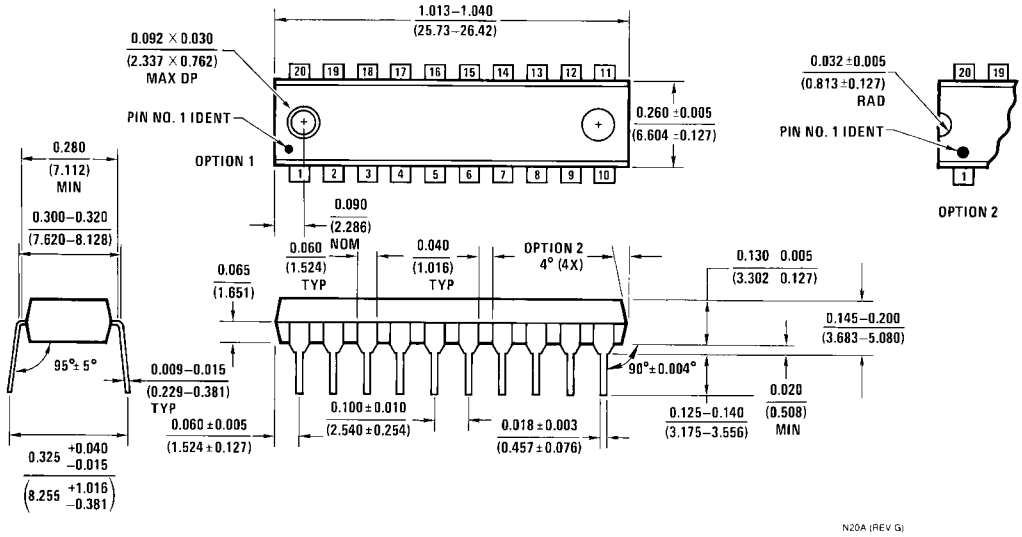
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1990
Revised November 1999

74ACQ574 • 74ACTQ574
Quiet Series™ Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACQ/ACTQ574 is a high-speed, low-power octal D-type flip-flop with a buffered Common Clock (CP) and a buffered common Output Enable ($\overline{OE}$). The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH clock (CP) transition.

ACQ/ACTQ574 utilizes FACT Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

The ACQ/ACTQ574 is functionally identical to the ACTQ374 but with different pin-out.

Features

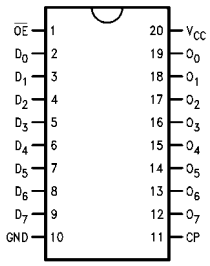
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of the package allowing easy interface with microprocessors
- Functionally identical to the ACQ/ACTQ374
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard AC/ACT574

Ordering Code:

Order Number	Package Number	Package Description
74ACQ574SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACQ574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACQ574PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
74ACTQ574SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACTQ574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ574PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix “X” to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

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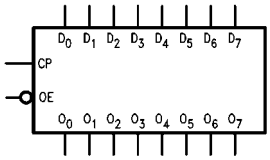
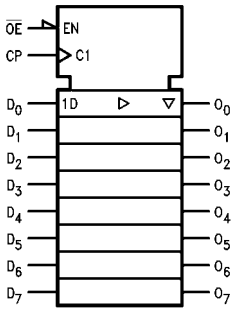
Logic Symbols



IEEE/IEC



Functional Description

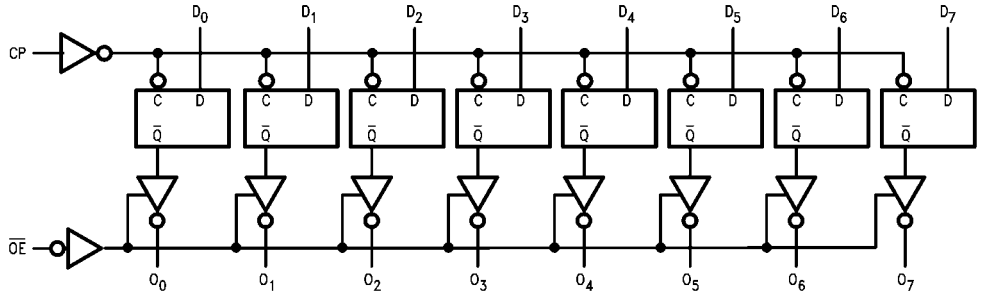
The ACQ/ACTQ574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O_N	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	⌐	L	L	Z	Load
H	⌐	H	H	Z	Load
L	⌐	L	L	L	Data Available
L	⌐	H	H	H	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level	3.0	2.99	2.9	2.9		
	Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	3.0	0.002	0.1	0.1		
	Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	–0.6	–1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 7: Maximum number of data inputs (n) switching. (n–1) inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
		4.5		3.85	3.76	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 8)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	µA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 9)	5.5			–75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	–0.6	–1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package.

Note 11: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

DC Electrical Characteristics for ACTQ (Continued)

Note 12: Max number of data inputs (n) switching. (n–1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	3.3	75			70		MHz
		5.0	90			85		
t_{PLH}	Propagation Delay	3.3	3.0	9.5	13.0	3.0	13.5	ns
t_{PHL}	CP to $\overline{O}_n$	5.0	2.0	6.5	8.5	2.0	9.0	
t_{PZH}	Output Enable Time	3.3	3.0	9.5	13.0	3.0	13.5	ns
t_{PZL}		5.0	2.0	6.5	8.5	2.0	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	9.5	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	8.0	9.5	1.0	10.0	
t_{OSHL}	Output to Output Skew (Note 14)	3.3		1.0	1.5		1.5	ns
t_{OSLH}	CP to $\overline{O}_n$	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACQ

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	0	3.0	3.0	ns
	D_n to CP	5.0	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	0	1.5	1.5	ns
	D_n to CP	5.0	0	1.5	1.5	
t_W	CP Pulse Width,	3.3	2.0	4.0	4.0	ns
	HIGH or LOW	5.0	2.0	4.0	4.0	

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Voltage Range 3.3 is 3.3V ± 0.3V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	85			80		MHz
t_{PLH}	Propagation Delay	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PHL}	CP to $\overline{O}_n$							
t_{PZH}	Output Enable	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PZL}	Time							
t_{PHZ}	Output Disable	5.0	1.0	8.0	10.0	1.0	10.5	ns
t_{PLZ}	Time							
t_{OSHL}	Output to Output Skew (Note 17)	5.0		0.5	1.0		1.0	ns
t_{OSLH}	CP to $\overline{O}_n$							

Note 16: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 18)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	1.5	1.5	ns
t_W	CP Pulse Width, HIGH or LOW	5.0	2.0	4.0	4.0	ns

Note 18: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

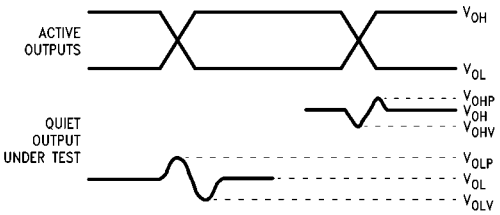
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 19: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 20: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case for active and enable transition. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

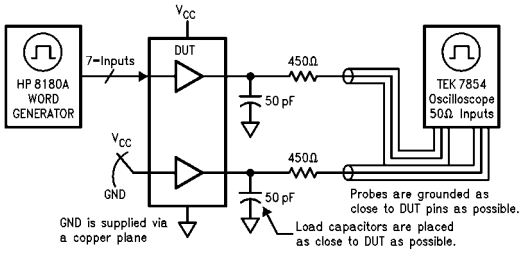
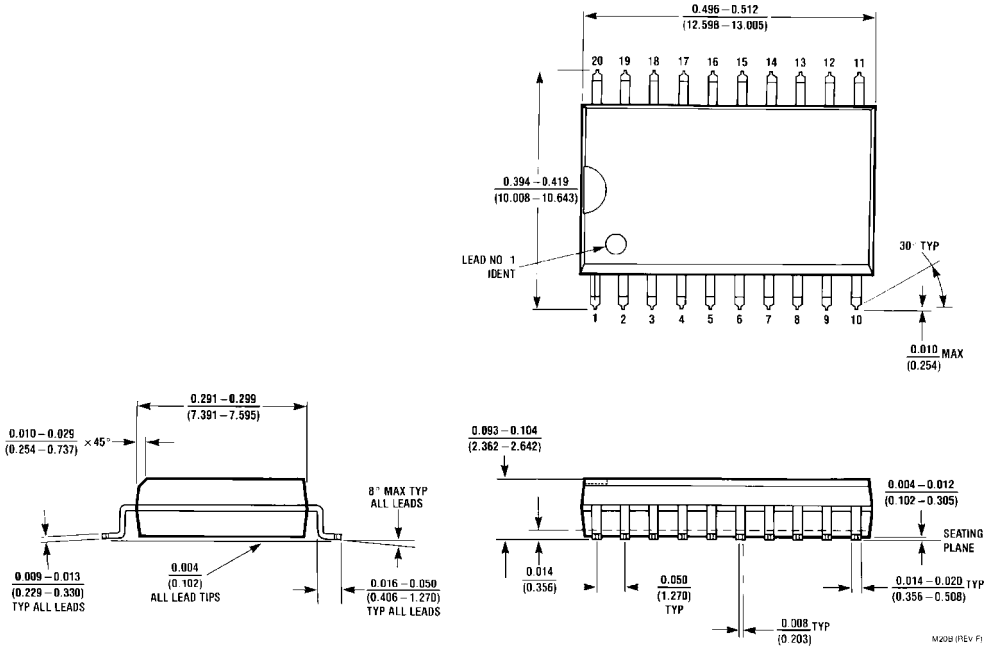


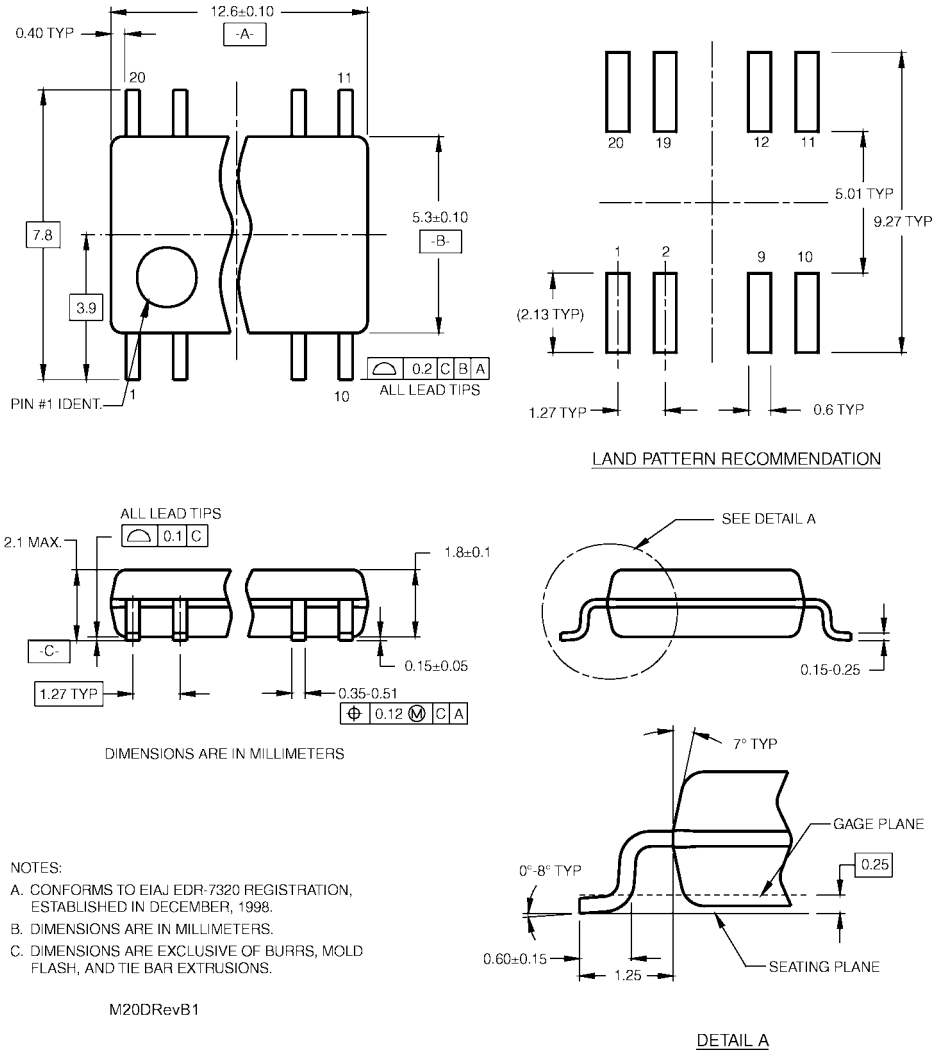
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

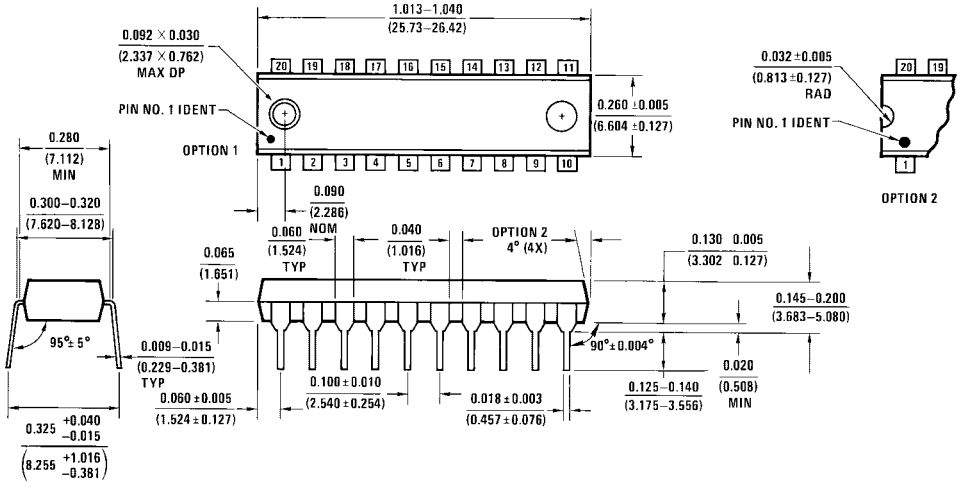
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1990
Revised December 1998

74ACQ646 • 74ACTQ646 Quiet Series™ Octal Transceiver/Register with 3-STATE Outputs

General Description

The ACQ/ACTQ646 consist of registered bus transceiver circuits, with outputs, D-type flip-flops, and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate clock pin (CPAB or CPBA). The four fundamental handling functions available are illustrated in Figure 1, Figure 2, Figure 3 and Figure 4.

The ACQ/ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

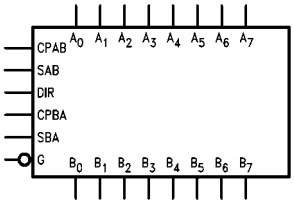
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Independent registers for A and B busses
- Multiplexed real-time and stored data transfers
- 300 mil slim dual-in-line package
- Outputs source/sink 24 mA
- Faster prop delays than the standard AC/ACT646

Ordering Code:

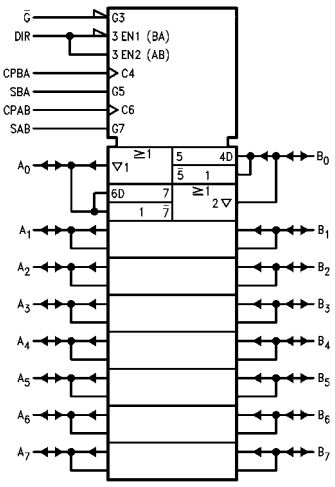
Order Number	Package Number	Package Description
74ACQ646SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
74ACQ464ASPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300” Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

Logic Symbols



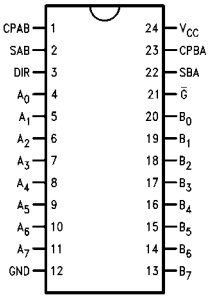
IEEE/IEC



FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation

Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Descriptions
A_0–A_7	Data Register A Inputs
	Data Register A Outputs
B_0–B_7	Data Register B Inputs
	Data Register B Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
$\overline{G}$	Output Enable Input
DIR	Direction Control Input

Function Table

Inputs						Data I/O (Note 1)		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

Real Time Transfer A-Bus to B-Bus

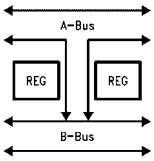


FIGURE 1.

Real Time Transfer B-Bus to A-Bus

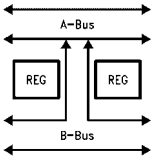


FIGURE 2.

Storage from Bus to Register

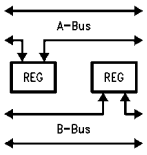


FIGURE 3.

Transfer from Register to Bus

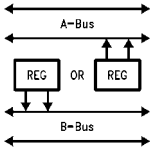
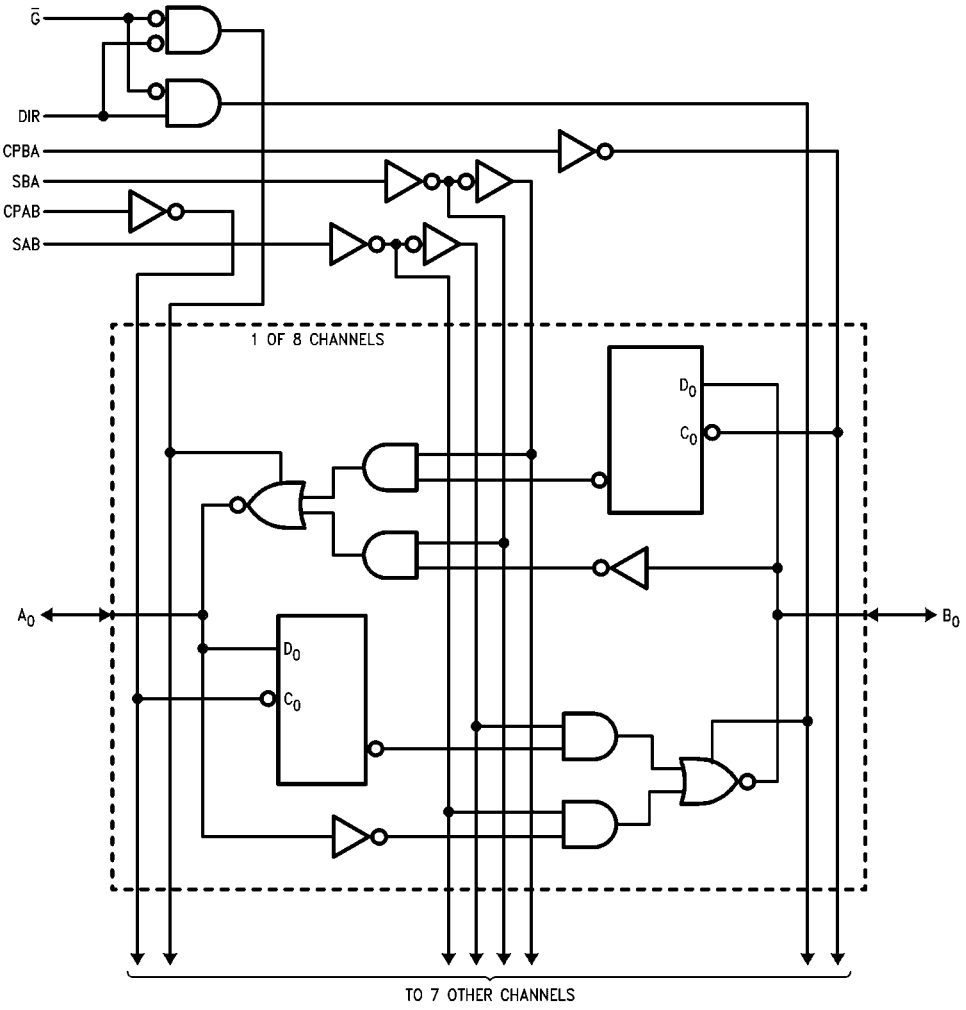


FIGURE 4.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source	
or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.85	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{IN} (Note 5)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 5)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current (A_n, B_n Inputs)	5.5		±0.6	±6.0	μA	V_I(OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 5, Figure 6 (Note 6)(Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 5, Figure 6 (Note 6)(Note 7)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 6)(Note 8)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 6)(Note 8)

Note 3: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 6: Plastic DIP package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 5V (ACQ). Input-under-test switching 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}) f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 9)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 9)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZT}	Maximum I/O Leakage Current (A_n, B_n Inputs)	5.5		±0.6	±6.0	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 10)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 5, Figure 6 (Note 6)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	–0.6	–1.2		V	Figure 5, Figure 6 (Note 6)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.7	2.0		V	(Note 6)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 6)(Note 12)

Note 9: All outputs loaded; thresholds on input associated with output under test.

Note 10: Maximum test duration 2.0 ms, one output loaded at a time.

DC Electrical Characteristics for ACTQ (Continued)

Note 11: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 12: Max number of data inputs (n) switching. (n − 1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	3.5	9.0	12.0	3.5	13.0	ns
	Bus to Bus	5.0	2.5	6.5	9.0	2.5	9.5	
t_{PHL}	Propagation Delay	3.3	3.5	9.0	12.0	3.5	13.0	ns
	Bus to Bus	5.0	2.5	6.5	9.0	2.5	9.5	
t_{PLH}	Propagation Delay	3.3	3.5	10.0	13.0	3.5	14.0	ns
	Clock to Bus	5.0	2.5	7.0	9.5	2.5	10.5	
t_{PHL}	Propagation Delay	3.3	3.5	10.0	13.0	3.5	14.0	ns
	Clock to Bus	5.0	2.5	7.0	9.5	2.5	10.5	
t_{PLH}	Propagation Delay	3.3	3.5	9.5	12.5	3.5	13.5	
	SBA or SAB to A_n or B_n	5.0	2.5	6.5	9.0	2.5	10.0	ns
	(w/A_n or B_n HIGH or LOW)							
t_{PHL}	Propagation Delay	3.3	3.5	9.5	12.5	3.5	13.5	
	SBA or SAB to A_n or B_n	5.0	2.5	6.5	9.0	2.5	10.0	ns
	(w/A_n or B_n HIGH or LOW)							
t_{PZH}	Enable Time	3.3	3.5	10.5	14.5	3.5	15.5	ns
	$\overline{G}$ to A_n or B_n	5.0	2.5	8.0	10.5	2.5	11.5	
t_{PZL}	Enable Time	3.3	3.5	10.5	14.5	3.5	15.5	ns
	$\overline{G}$ to A_n or B_n	5.0	2.5	8.0	10.5	2.5	11.5	
t_{PHZ}	Disable Time	3.3	2.5	8.0	11.0	2.5	12.0	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	5.0	7.5	1.5	8.0	
t_{PLZ}	Disable Time	3.3	2.5	8.0	11.0	2.5	12.0	ns
	$\overline{G}$ to A_n or B_n	5.0	1.5	5.0	7.5	1.5	8.0	
t_{PZH}	Enable Time	3.3	4.5	11.0	15.5	4.5	17.0	ns
	DIR to A_n or B_n	5.0	3.0	8.5	11.0	3.0	11.5	
t_{PZL}	Enable Time	3.3	4.5	11.0	15.5	4.5	17.0	ns
	DIR to A_n or B_n	5.0	3.0	8.5	11.0	3.0	11.5	
t_{PHZ}	Disable Time	3.3	1.5	8.0	11.0	1.5	12.0	ns
	DIR to A_n or B_n	5.0	1.0	5.0	7.5	1.0	8.0	
t_{PLZ}	Disable Time	3.3	1.5	8.0	11.0	1.5	12.0	ns
	DIR to A_n or B_n	5.0	1.0	5.0	7.5	1.0	8.0	
t_{OS}	Output to Output Skew (Note 14)	3.3		1.0	1.5		1.5	ns
		5.0		0.5	1.0		1.0	

Note 13: Voltage Range 3.3 is 3.3V ± 0.3V.
Voltage Range 5.0 is 5.0V ± 0.5V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for ACQ

Symbol	Parameter	V_{CC} (Note 15)(Note 16)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3		3.0	3.0	ns
	Bus to Clock	5.0		3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3		1.5	1.5	ns
	Bus to Clock	5.0		1.5	1.5	
t_W	Clock Pulse Width	3.3		4.0	4.0	ns
	HIGH or LOW	5.0		4.0	4.0	

Note 15: Voltage Range 3.3 is 3.3V ±0.3V.

Note 16: Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 17)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay Clock to Bus	5.0	2.5	8.5	10.5	2.5	11.0	ns
t_{PLH} t_{PHL}	Propagation Delay Bus to Bus	5.0	2.0	8.0	10.0	2.0	10.5	ns
t_{PLH} t_{PHL}	Propagation Delay SBA or SAB to A_n or B_n (w/A_n or B_n HIGH or LOW)	5.0	2.5	8.5	10.5	2.5	11.0	ns
t_{PZH} t_{PZL}	Enable Time $\overline{G}$ to A_n or B_n	5.0	2.5	10.0	12.0	2.5	12.5	ns
t_{PHZ} t_{PLZ}	Disable Time $\overline{G}$ to A_n or B_n	5.0	1.0	7.0	8.5	1.0	9.0	ns
t_{PZH} t_{PZL}	Enable Time DIR to A_n or B_n	5.0	2.5	10.0	12.0	2.5	12.5	ns
t_{PHZ} t_{PLZ}	Disable Time DIR to A_n or B_n	5.0	1.0	7.0	8.5	1.0	9.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 18) Select to Bus or Clock to Bus	5.0		0.5	1.0		1.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 18) Bus to Bus	5.0		1.0	1.5		1.5	ns

Note 17: Voltage Range 5.0 is 5.0V ±0.5V

Note 18: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 19)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW Bus to Clock	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW Bus to Clock	5.0		1.5	1.5	ns
t_W	Clock Pulse Width HIGH or LOW	5.0		4.0	4.0	ns

Note 19: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
$C_{I/O}$	Input/Output Capacitance	15.0	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	90.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

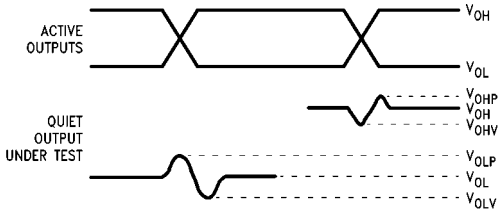


FIGURE 5. Quiet Output Noise Voltage Waveforms

Note 20: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 21: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL},until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

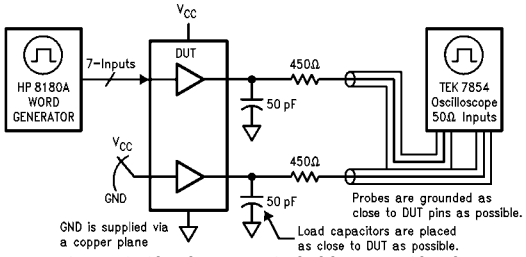
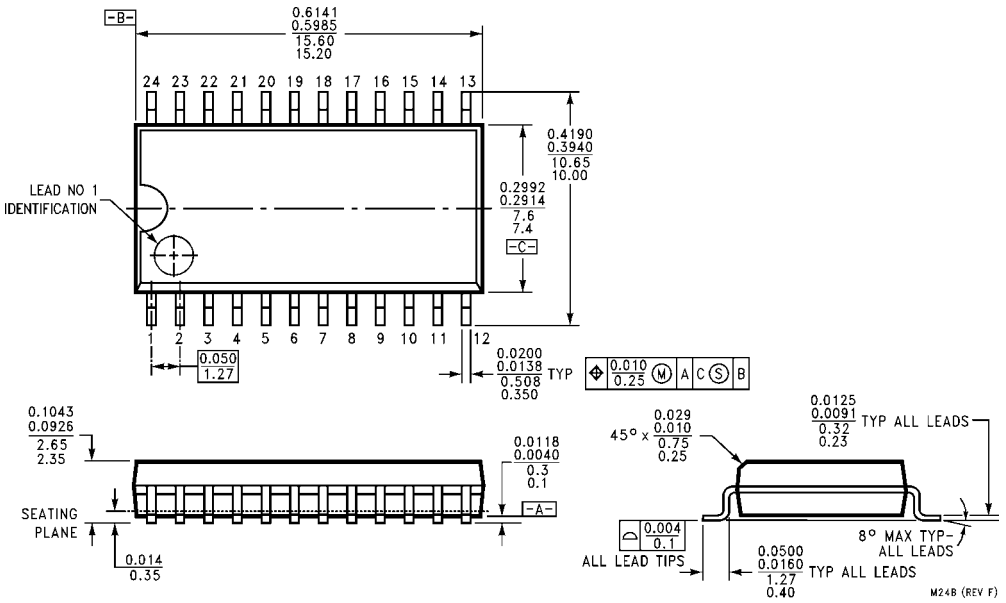


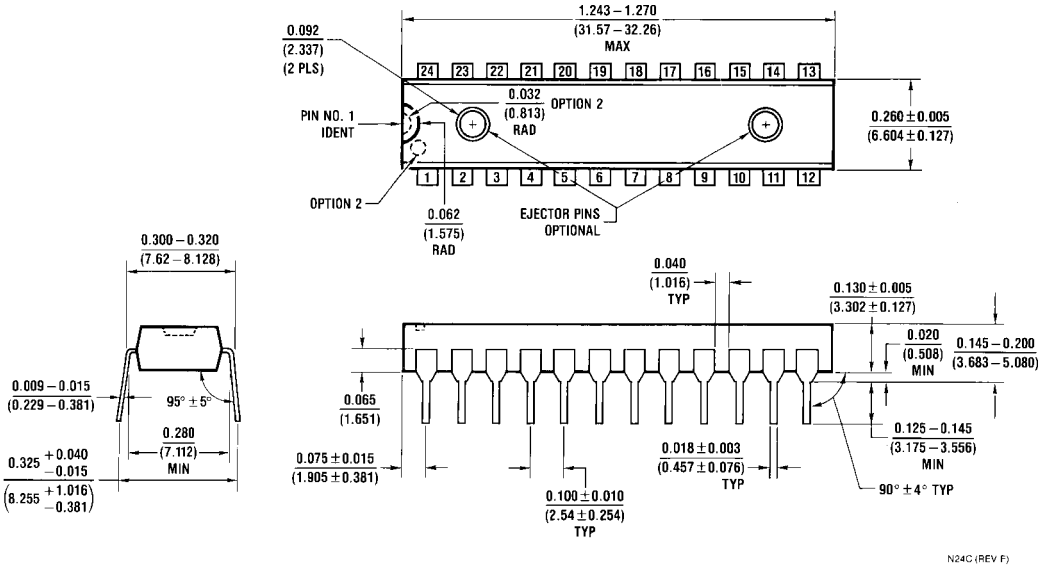
FIGURE 6. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Slim Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1990
Revised December 1999

74ACQ657 • 74ACTQ657
Quiet Series™ Octal Bidirectional Transceiver with 8-Bit Parity Generator/Checker and 3-STATE Outputs

General Description

The ACQ/ACTQ657 contains eight non-inverting buffers with 3-STATE outputs and an 8-bit parity generator/checker. Intended for bus oriented applications, the device combines the 245 and the 280 functions in one package.

The ACQ/ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus or superior performance.

Features

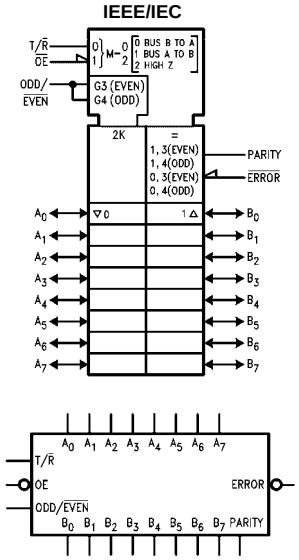
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Combines the 245 and the 280 functions in one package
- 300 mil 24-pin slim dual-in-line package
- Outputs source/sink 24 mA
- ACTQ has TTL-compatible inputs

Ordering Code:

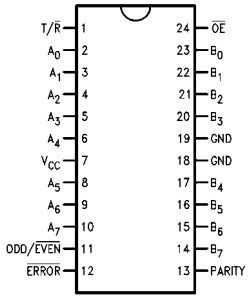
Order Number	Package Number	Package Description
74ACQ657SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
74ACTQ657SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ657SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7	Data Inputs/3-STATE Outputs
B_0–B_7	Data Inputs/3-STATE Outputs
T/$\overline{R}$	Transmit/Receive Input
$\overline{OE}$	Enable Input
PARITY	Parity Input/3-STATE Output
ODD/$\overline{EVEN}$	ODD/$\overline{EVEN}$ Parity Input
$\overline{ERROR}$	Error 3-STATE Output

FACT™, Quiet Series™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

The Transmit/Receive (T/$\overline{R}$) input determines the direction of the data flow through the bidirectional transceivers. Transmit (active HIGH) enables data from the A-Port to the B-Port; Receive (active LOW) enables data from the B-Port to the A-Port.

The Output Enable ($\overline{OE}$) input disables the parity and $\overline{ERROR}$ outputs and both the A and B Ports by placing them in a HIGH-Z condition when the Output Enable input is HIGH.

When transmitting (T/$\overline{R}$ HIGH), the parity generator detects whether an even or odd number of bits on the A-Port are HIGH and compares these with the condition of the parity select (ODD/$\overline{EVEN}$). If the Parity Select is HIGH and an even number of A inputs are HIGH, the Parity output is HIGH.

In receiving mode (T/$\overline{R}$ LOW), the parity select and number of HIGH inputs on port B are compared to the condition of the Parity input. If an even number of bits on the B-Port are HIGH, the parity select is HIGH, and the PARITY input is HIGH, then $\overline{ERROR}$ will be HIGH to indicate no error. If an odd number of bits on the B-Port are HIGH, the parity select is HIGH, and the PARITY input is HIGH, the $\overline{ERROR}$ will be LOW indicating an error.

Function Table

Number of Inputs That Are High	Inputs			Input/ Output	Outputs	
	$\overline{OE}$	T/$\overline{R}$	ODD/$\overline{EVEN}$	Parity	$\overline{ERROR}$	Outputs Mode
0, 2, 4, 6, 8	L	H	H	H	Z	Transmit
	L	H	L	L	Z	Transmit
	L	L	H	H	H	Receive
	L	L	H	L	L	Receive
	L	L	L	H	L	Receive
	L	L	L	L	H	Receive
1, 3, 5, 7	L	H	H	L	Z	Transmit
	L	H	L	H	Z	Transmit
	L	L	H	H	L	Receive
	L	L	H	L	H	Receive
	L	L	L	H	H	Receive
	L	L	L	L	L	Receive
Immaterial	H	X	X	Z	Z	Z

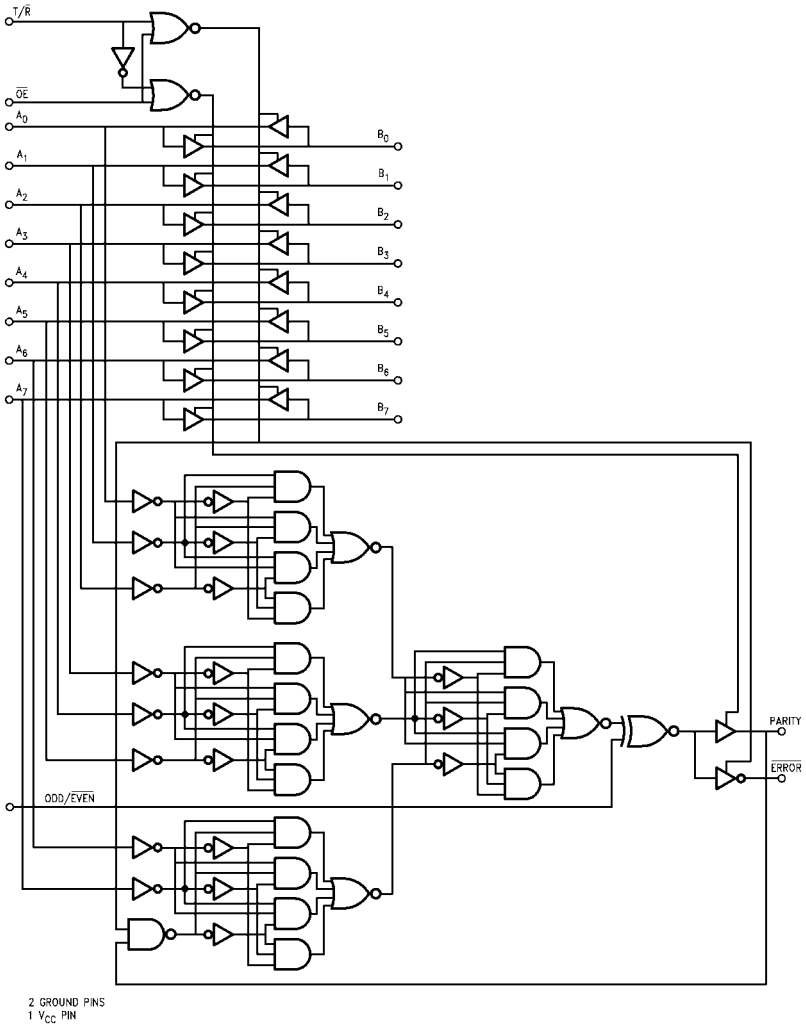
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Function Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 MA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O =V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC}or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source	
Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	3.0	1.5	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum LOW Level Input Voltage	3.0	1.5	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum HIGH Level Voltage Output	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46	V	I_{OH} = −12 mA
		4.5		3.86	3.76		I_{OH} = −24mA
		5.5		4.85	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44	V	I_{OL} = 12 mA
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current ($T/\overline{R}$, $\overline{OE}$, ODD/$\overline{EVEN}$ Inputs)	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current (A_n, B_n Inputs)	5.5		±0.6	±6.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND

DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Note 5)(Note 7)

Note 2: Maximum of 8 outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 5: DIP package.

Note 6: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of Data Inputs (n) switching. (n−1) Inputs switching 0V to 5V (ACQ).Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}) f = 1 MHz.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OH} = −24mA I_{OH} = −24 mA (Note 8)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL}$ or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 8)
I_{IN}	Maximum Input Leakage Current (T/$\overline{R}$, $\overline{OE}$, ODD/$\overline{EVEN}$ Inputs)	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{OZT}	Maximum I/O Leakage Current (A_n, B_n Inputs)	5.5 5.5		±0.6	±6.0	μA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 9)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 10)(Note 11)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 10)(Note 12)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 10)(Note 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: DIP package.

Note 11: Max number of outputs defined as (n). n−1 Data Inputs are driven 0V to 3V; one output @ GND.

Note 12: Max number of Data Inputs (n) switching. (n−1) Inputs switching 0V to 3V (ACQ). Input-under-test switching; 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}) f =1 MHz.

AC Electrical Characteristics for ACQ

Symbol	Parameter	V_{CC} (V) (Note 13)	$T_A = 25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.3	2.5	8.0	11.5	2.5	12.0	ns
t_{PHL}	A_n to B_n, B_n to A_n	5.0	1.5	5.0	7.5	1.5	8.0	
t_{PLH}	Propagation Delay	3.3	3.0	11.5	16.5	3.0	17.0	ns
t_{PHL}	A_n to Parity	5.0	2.0	7.0	10.5	2.0	11.0	
t_{PLH}	Propagation Delay	3.3	3.0	10.0	15.0	3.0	15.5	ns
t_{PHL}	ODD/$\overline{\text{EVEN}}$ to PARITY	5.0	2.5	6.5	10.0	2.5	10.5	
t_{PLH}	Propagation Delay	3.3	3.0	10.0	15.0	3.0	15.5	ns
t_{PHL}	ODD/$\overline{\text{EVEN}}$ to $\overline{\text{ERROR}}$	5.0	2.5	6.5	10.0	2.5	10.5	
t_{PLH}	Propagation Delay	3.3	3.5	11.5	16.0	3.5	16.5	ns
t_{PHL}	B_n to $\overline{\text{ERROR}}$	5.0	2.5	7.0	10.5	2.5	11.0	
t_{PLH}	Propagation Delay	3.3	3.0	9.0	13.5	3.0	14.0	ns
t_{PHL}	PARITY to $\overline{\text{ERROR}}$	5.0	2.0	6.0	9.0	2.0	9.5	
t_{PZH}	Output Enable Time	3.3	2.5	9.0	13.5	2.5	14.0	ns
t_{PZL}	$\overline{OE}$ to A_n/B_n	5.0	2.0	6.0	9.0	2.0	9.5	
t_{PHZ}	Output Disable Time	3.3	1.0	8.5	13.0	1.0	13.5	ns
t_{PLZ}	$\overline{OE}$ to A_n/B_n	5.0	1.0	5.5	8.5	1.0	9.0	
t_{PZH}	Output Enable Time	3.3	2.5	9.0	13.5	2.5	14.0	ns
t_{PZL}	$\overline{OE}$ to $\overline{\text{ERROR}}$ (Note 15)	5.0	2.0	6.0	9.0	2.0	9.5	
t_{PHZ}	Output Disable Time	3.3	1.0	8.5	13.0	1.0	13.5	ns
t_{PLZ}	$\overline{OE}$ to $\overline{\text{ERROR}}$	5.0	1.0	5.5	8.5	1.0	9.0	
t_{PZH}	Output Enable Time	3.3	2.5	9.0	13.5	2.5	14.0	ns
t_{PZL}	$\overline{OE}$ to PARITY	5.0	2.0	6.0	9.0	2.0	9.5	
t_{PHZ}	Output Disable Time	3.3	1.0	8.5	13.0	1.0	13.5	ns
t_{PLZ}	$\overline{OE}$ to PARITY	5.0	1.0	5.5	8.5	1.0	9.0	
t_{OSHL}	Output to Output Skew (Note 14)	3.3		1.0	1.5		1.5	ns
t_{OSLH}	A_n, B_n to B_n, A_n	5.0		0.5	1.0		1.0	

Note 13: Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

Note 15: These delay times reflect the 3-STATE recovery time only and not the signal time through the buffers or the parity check circuitry. To assure VALID information at the $\overline{\text{ERROR}}$ pin, time must be allowed for the signal to propagate through the drivers (B to A), through the parity check circuitry (same as A to PARITY), and to the $\overline{\text{ERROR}}$ output after the $\overline{\text{ERROR}}$ pin has been enabled (Output Enable times). VALID data at the $\overline{\text{ERROR}}$ pin ≥ (A to PARITY) +(Output Enable Time).

AC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V) (Note 16)	$T_A = 25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n to B_n, B_n to A_n	5.0	1.5	5.0	8.0	1.5	8.5	ns
t_{PLH} t_{PHL}	Propagation Delay A_n to Parity	5.0	2.5	7.5	11.0	2.5	11.5	ns
t_{PLH} t_{PHL}	Propagation Delay ODD/$\overline{\text{EVEN}}$ to PARITY	5.0	2.5	6.5	10.5	2.5	11.0	ns
t_{PLH} t_{PHL}	Propagation Delay ODD/$\overline{\text{EVEN}}$ to $\overline{\text{ERROR}}$	5.0	2.5	6.5	10.5	2.5	11.0	ns
t_{PLH}, t_{PHL}	Propagation Delay B_n to $\overline{\text{ERROR}}$	5.0	3.0	7.5	11.0	3.0	11.5	ns
t_{PLH} t_{PHL}	Propagation Delay PARITY to $\overline{\text{ERROR}}$	5.0	2.0	6.0	9.5	2.0	10.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to A_n/B_n	5.0	2.0	6.0	9.5	2.0	10.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to A_n/B_n	5.0	1.0	5.0	9.0	1.0	9.5	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to $\overline{\text{ERROR}}$ (Note 18)	5.0	2.0	6.0	9.5	2.0	10.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to $\overline{\text{ERROR}}$	5.0	1.0	6.0	9.0	1.0	9.5	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to PARITY	5.0	2.0	6.0	9.5	2.0	10.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to PARITY	5.0	1.0	5.0	9.0	1.0	9.5	ns
t_{OSHL} t_{OSLH}	Output to Output Skew A_n, B_n to B_n, A_n (Note 17)	5.0		0.5	1.0		1.0	ns

Note 16: Voltage Range 5.0 is 5.0V ±0.5V

Note 17: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

Note 18: These delay times reflect the 3-STATE recovery time only and not the signal time through the buffers or the parity check circuitry. To assure VALID information at the $\overline{\text{ERROR}}$ pin, time must be allowed for the signal to propagate through the drivers (B to A), through the parity check circuitry (same as A to PARITY), and to the $\overline{\text{ERROR}}$ output after the $\overline{\text{ERROR}}$ pin has been enabled (Output Enable times). VALID data at the $\overline{\text{ERROR}}$ pin ≥ (A to PARITY) + (Output Enable Time).

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	160.0	pF	$V_{CC} = 5.0$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

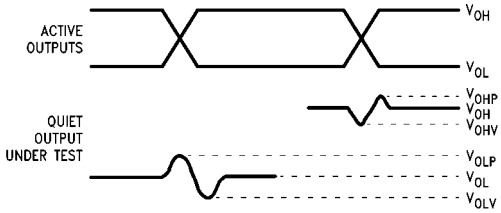


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 19: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 20: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

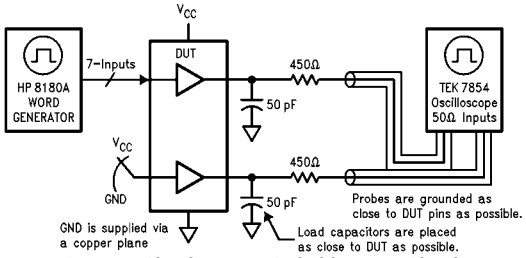
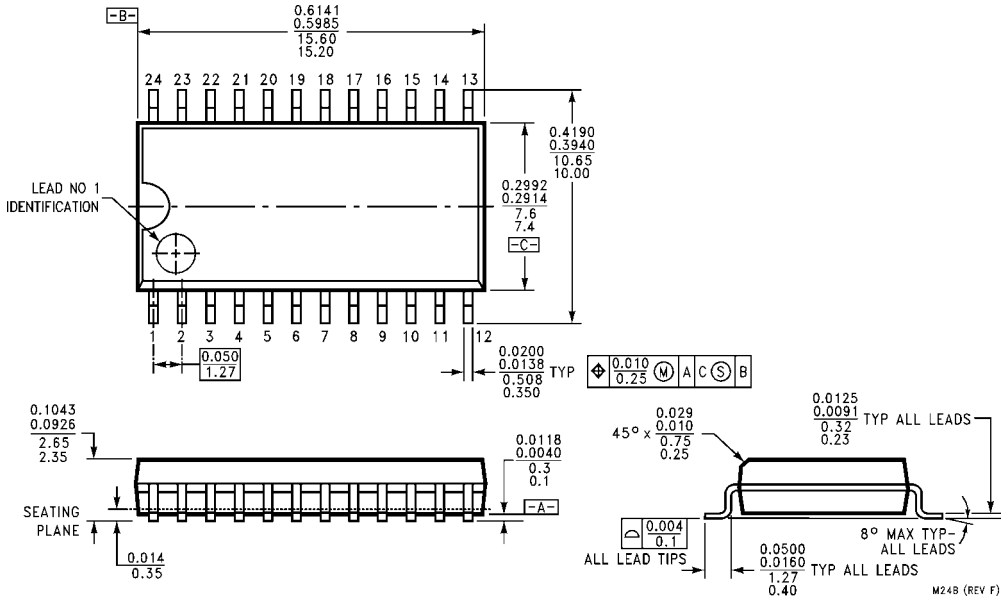


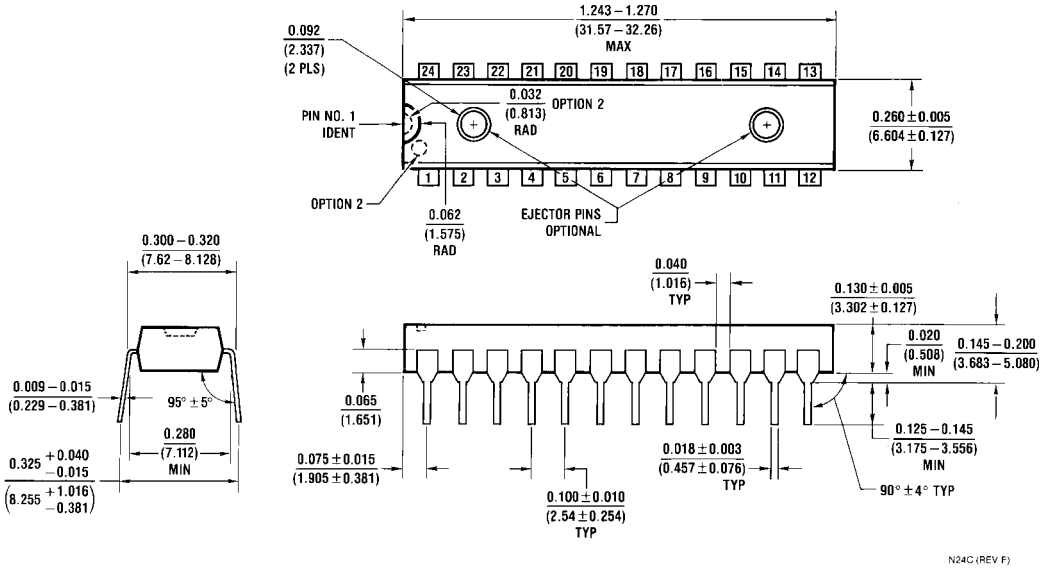
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

June 1996
Revised November 1999

74ACT1284
IEEE 1284 Transceiver

General Description

The 74ACT1284 contains four non-inverting bidirectional buffers and three non-inverting buffers with open Drain outputs and high drive capability on the B Ports. It is intended to provide a standard signaling method for a bi-direction parallel peripheral in an Extended Capabilities Port mode (ECP).

The HD (active HIGH) input pin enables the B Ports to switch from open Drain to a high drive totem pole output, capable of sourcing 14 mA on all seven buffers. The DIR input determines the direction of data flow on the bidirectional buffers. DIR (active HIGH) enables data flow from A Ports to B Ports. DIR (active LOW) enables data flow from B Ports to A Ports.

Features

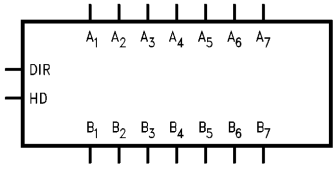
- TTL-compatible inputs
- A Ports have standard 4 mA totem pole outputs
- Typical input hysteresis of 0.5V
- B Port high drive source/sink capability of 14 mA
- Bidirectional non-inverting buffers
- Supports IEEE P1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals
- B Port outputs in High Impedance mode during power down
- Guaranteed 4000V minimum ESD protection

Ordering Code:

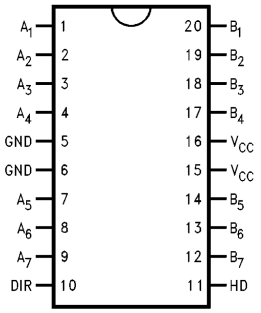
Order Number	Package Number	Package Description
74ACT1284SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74ACT1284MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ACT1284MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
HD	High Drive Enable input (Active HIGH)
DIR	Direction Control Input
A_1 - A_4	Side A Inputs or Outputs
B_1 - B_4	Side B Inputs or Outputs
A_5 - A_7	Side A Inputs
B_5 - B_7	Side B Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

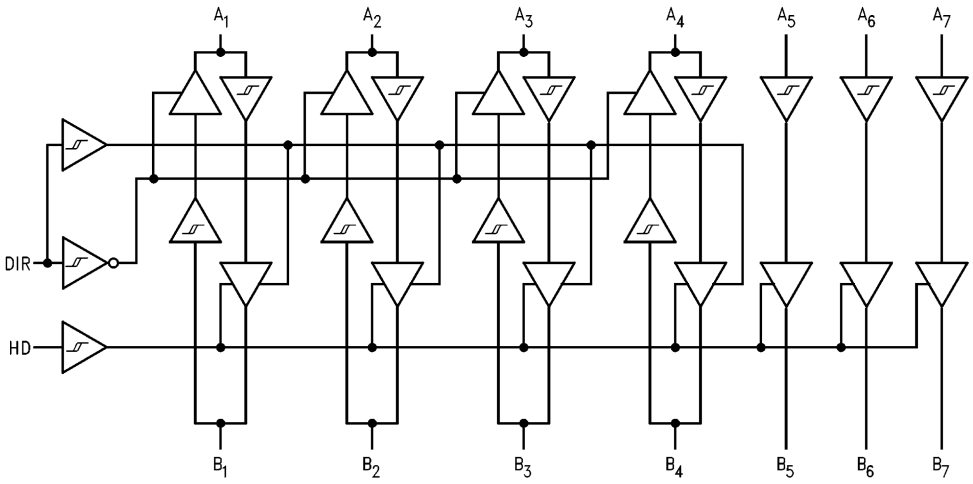
Truth Table

Inputs		Outputs
DIR	**HD**	
L	L	B_1- B_4 Data to A_1 - A_4, and A_5 - A_7 Data to B_5 - B_7 (Note 1)
L	H	B_1- B_4 Data to A_1 - A_4, and A_5 - A_7 Data to B_5 - B_7
H	L	A_1 - A_7 Data to B_1 - B_7 (Note 2)
H	H	A_1 - A_7 Data to B_1 - B_7

Note 1: B_5 - B_7 Open Drain Outputs

Note 2: B_1 - B_7 Open Drain Outputs

Logic Diagram



Absolute Maximum Ratings(Note 3)

(Note 4)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I) A Side	−0.5V to V_{CC} + 0.5V
DC Input Voltage (V_I) B Side	−2V to +7V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O) A Side	−0.5V to V_{CC} + 0.5V
DC Output Voltage (V_O) B Side	−2V to +7V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.7V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C

Note 3: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	Guaranteed Limits			Units	Conditions
			$T_A = +25°C$	$T_A = 0°C$ to $+70°C$	$T_A = -40°C$ to $+85°C$		
V_{IH}	Minimum HIGH Level Input Voltage	4.7	2.0	2.0	2.0	V	Recognized
		5.5	2.0	2.0	2.0		High Signal
V_{IL}	Maximum LOW Level Input Voltage	4.7	0.8	0.8	0.8	V	Recognized
		5.5	0.8	0.8	0.8		Low Signal
V_{OH}	Minimum HIGH Level Output Voltage	4.7	4.5	4.5	4.5	V	$I_{OUT} = -50$ µA (An) $V_{IN} = V_{IL}$ or V_{IH} (Note 5)
		4.7	3.7	3.7	3.7		$I_{OH} = -4$ mA (A_n)
		4.7	2.4	2.4	2.4	V	$I_{OH} = -14$ mA (B_n)
V_{OL}	Maximum LOW Level Output Voltage	4.7	0.2	0.2	0.2	V	$I_{OUT} = 50$ µA (An) $V_{IN} = V_{IL}$ or V_{IH} (Note 5)
		4.7	0.4	0.4	0.4		$I_{OH} = 4$ mA (A_n)
						V	$I_{OH} = 14$ mA (B_n)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND (DIR, A5, A6, A7, HD)
I_{CCT}	Maximum I_{CC}/Input	5.5		1.5	1.5	mA	$V_I = V_{CC} - 2.1V$
I_{CC}	Maximum Quiescent Supply Current	5.5	400	400	500	µA	$V_{IN} = V_{CC}$ or GND
I_{OZ}	Maximum Output Leakage Current	5.5	±20	±20	±20	µA	$V_O = V_{CC}$, GND
I_{OFF}	Maximum B-Side Power Down Leakage Current	0.0	100	100	100	µA	$V_{OUT} = 5.25V$
Δ_{VT}	Input Hysteresis	5.0	0.4	0.4	0.35	V	$V_{T+} - V_{T-}$
R_D	Maximum Output Impedance	5.0	22	22	24	Ω	B_n (Note 6)
	Minimum Output Impedance	5.0	8	8	6	Ω	B_n (Note 6)

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: This parameter is guaranteed but not tested, characterized only: RD is the measure of the B-Side output impedance with the output in the HIGH state.

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = 4.7V - 5.5V$		$T_A = 0°C$ to $+70°C$ $V_{CC} = 4.7V - 5.5V$		$T_A = -40°C$ to $+85°C$ $V_{CC} = 4.7V - 5.5V$		Units	Figure Number
		Min	Max	Min	Max	Min	Max		
t_{PHL}	A_1- A_7 to B_1 - B_7	2.0	20.0	2.0	20.0	2.0	24.0	ns	Figure 1
t_{PLH}	A_1- A_7 to B_1 - B_7	2.0	20.0	2.0	20.0	2.0	24.0	ns	Figure 2
t_{PHL}	B_1 - B_4 to A_1 - A_4	2.0	20.0	2.0	20.0	2.0	24.0	ns	Figure 3
t_{PLH}	B_1 - B_4 to A_1 - A_4	2.0	20.0	2.0	20.0	2.0	24.0	ns	Figure 3
$t_{pEnable}$	Output Enable Time HD to B_1 - B_7	2.0	20.0	2.0	20.0	2.0	24.0	ns	Figure 2
$t_{pDisable}$	Output Disable Time HD to B_1 - B_7	2.0	20.0	2.0	20.0	2.0	24.0	ns	Figure 2
t_{SKEW} t_{PLH} t_{PHL}	Output Slew Rate B_1 - B_7	0.05	0.40	0.05	0.40	0.05	0.40	V/ns	Figure 1 Figure 2
t_r, t_f	t_{RISE} and t_{FALL} B_1 - B_7 (Note 7)		120		120		120	ns	Figure 4 (Note 8)

Note 7: Open Drain

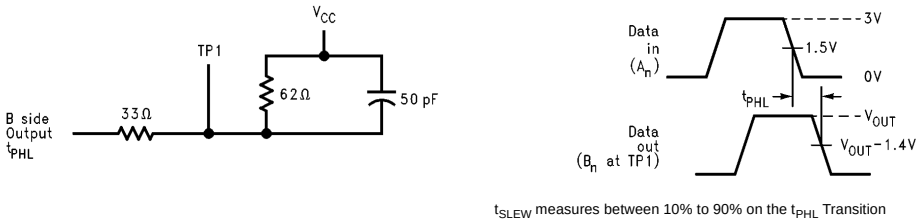
Note 8: This parameter is guaranteed but not tested, characterized only.

Note: Pulse Generator for all pulses; Rate $\leq$ 1.0 MHz; $A_O \leq 50\Omega$; $t_f \leq 2.5$ ns, $t_r \leq 2.5$ ns.

Capacitance

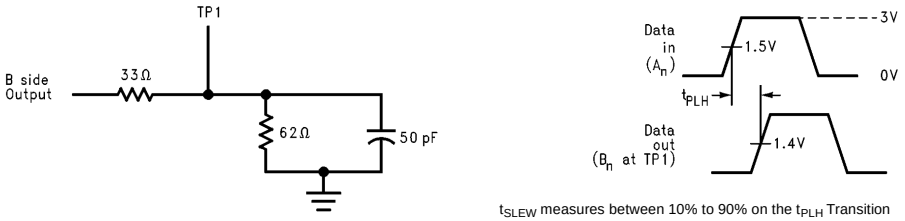
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.0	pF	V_{CC} = OPEN (HD, DIR A_5 - A_7)
$C_{I/O}$	I/O Pin Capacitance	12.0	pF	V_{CC} = 5.0V

AC Loading and Waveforms



t_{SLEW} measures between 10% to 90% on the t_{PHL} Transition

FIGURE 1. A to B Direction Test Load and Waveforms



t_{SLEW} measures between 10% to 90% on the t_{PLH} Transition

FIGURE 2. B Output Test Load and Waveforms

FIGURE 3. B to A Direction Test Load and Waveforms for Outputs A_1 - A_4

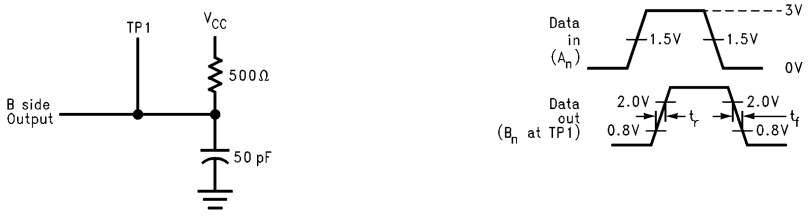
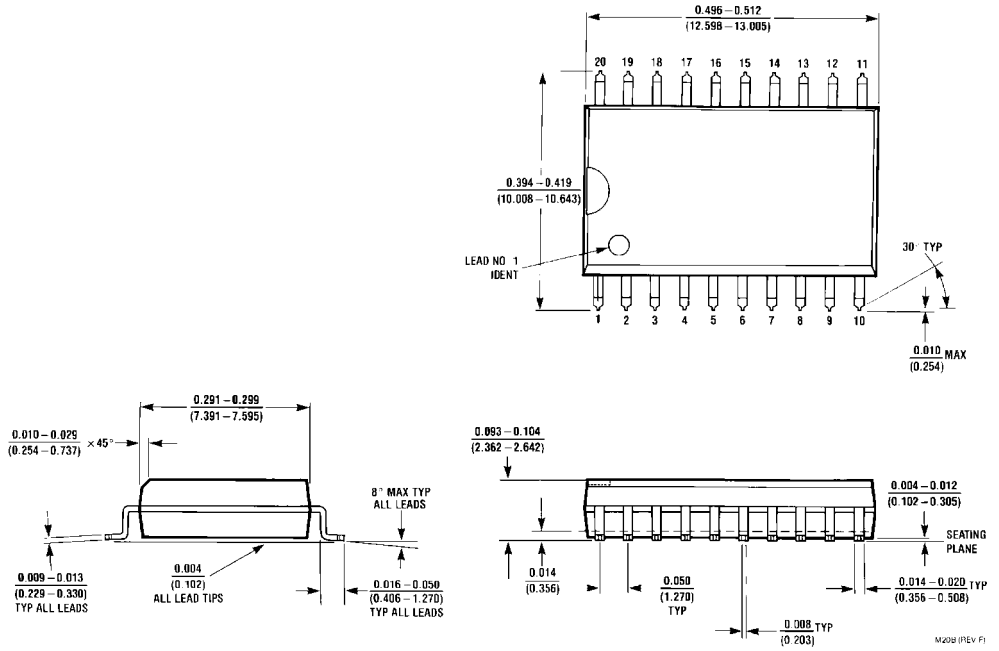
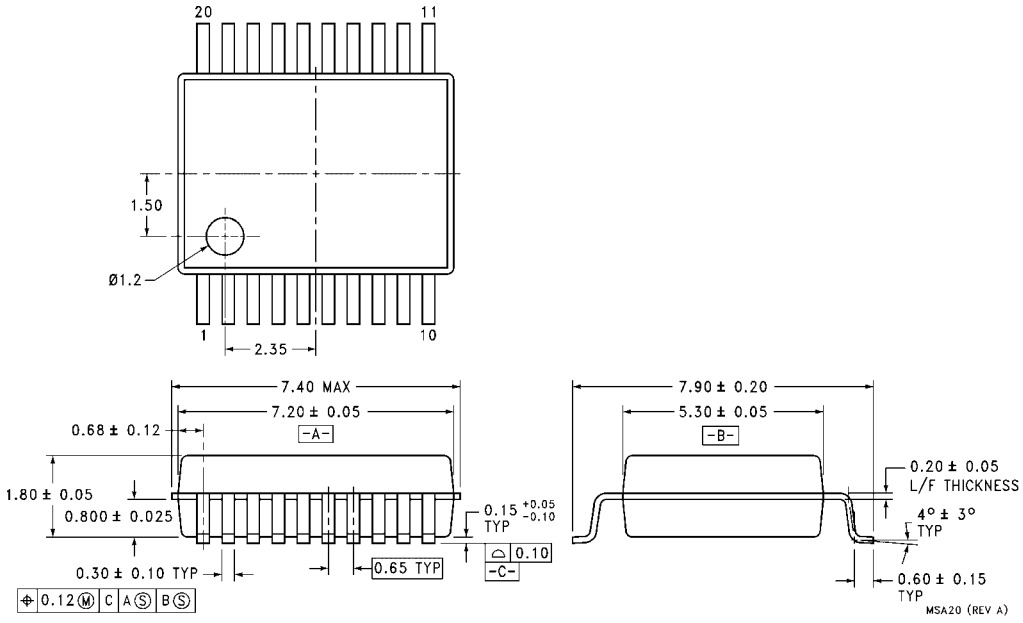


FIGURE 4. A to B Direction Test Load and Waveforms for Open Drain B_1 - B_7

Physical Dimensions inches (millimeters) unless otherwise noted

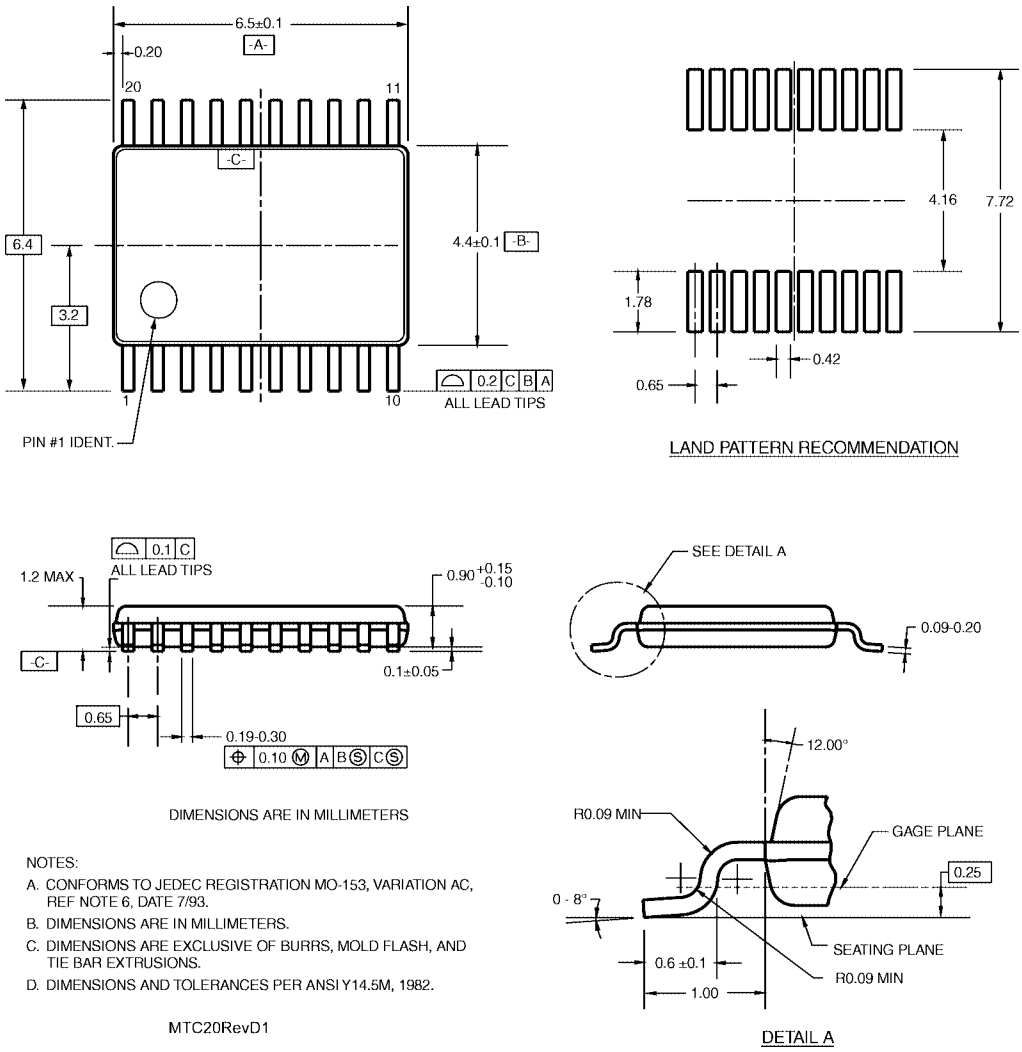


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74ACT158
Quad 2-Input Multiplexer

General Description

The ACT158 is a high-speed quad 2-input multiplexer. It selects four bits of data from two sources using the common Select and Enable inputs. The four buffered outputs present the selected data in the inverted form. The ACT158 can also be used as a function generator.

Features

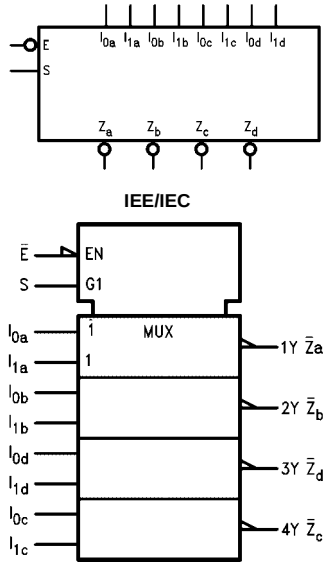
- I_{CC} reduced by 50%
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

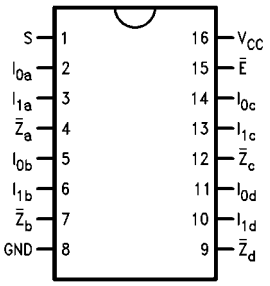
Order Number	Package Number	Package Description
74ACT158SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT158PC	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT158MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT158SJ	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{E}$	Enable Input
S	Select Input
$\overline{Z}_a$–$\overline{Z}_d$	Inverted Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT158 quad 2-input multiplexer selects four bits of data from two sources under the control of a common Select input (S) and presents the data in inverted form at the four outputs. The Enable input ($\overline{E}$) is active-LOW. When $\overline{E}$ is HIGH, all of the outputs ($\overline{Z}$) are forced HIGH regardless of all other inputs. The ACT158 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input.

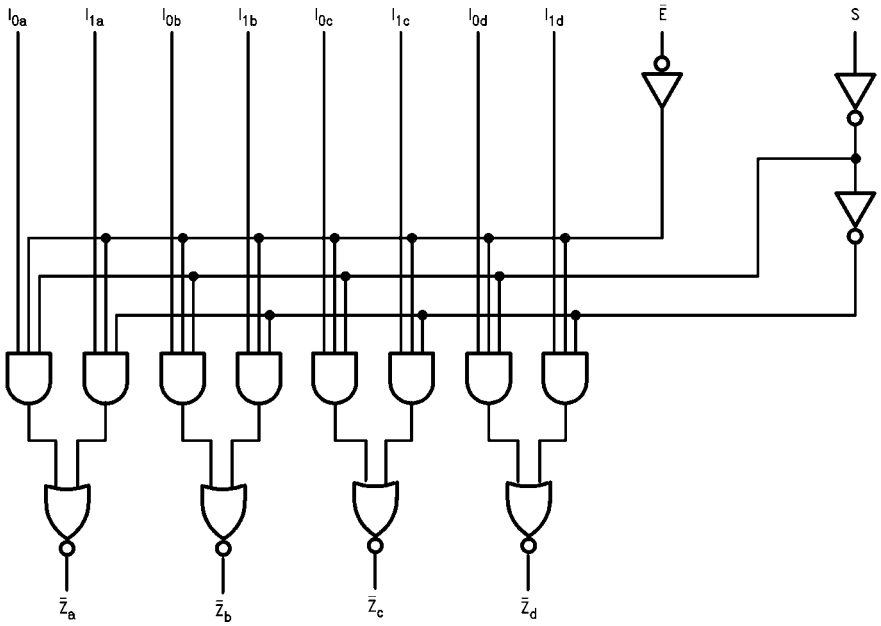
A common use of the ACT158 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The ACT158 can generate four functions of two variables with one variable common. This is useful for implementing gating functions.

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	$\overline{Z}$
H	X	X	X	H
L	L	L	X	H
L	L	H	X	L
L	H	X	L	H
L	H	X	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variable. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
						V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76		$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
						V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44		$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

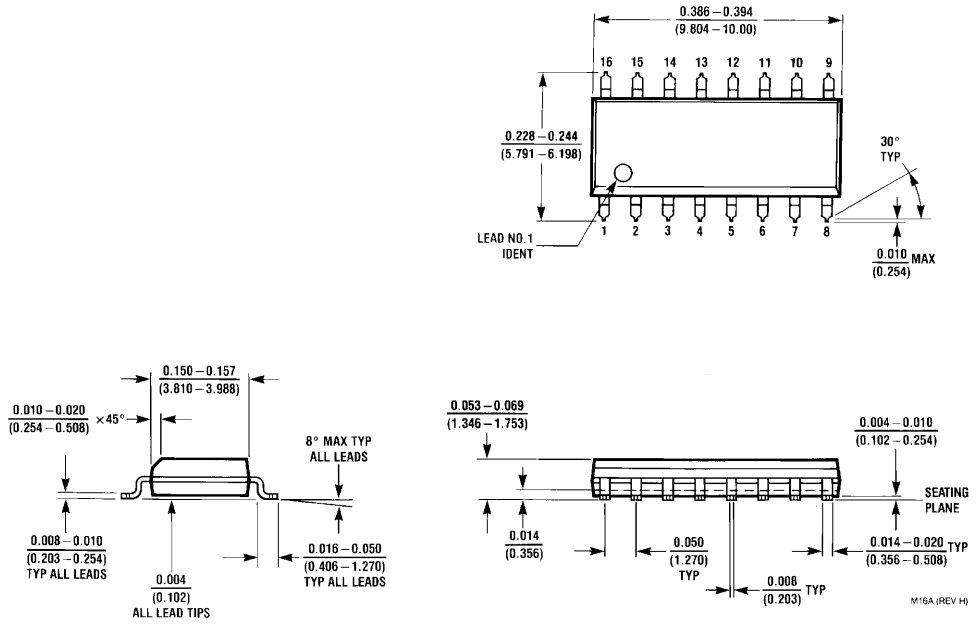
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S to $\overline{Z}_n$	5.0	2.5	6.0	9.5	2.0	11.0	ns
t_{PHL}	Propagation Delay S to $\overline{Z}_n$	5.0	1.5	5.5	9.0	1.5	10.0	ns
t_{PLH}	Propagation Delay $\overline{E}$ to $\overline{Z}_n$	5.0	1.5	5.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{E}$ to $\overline{Z}_n$	5.0	1.5	5.5	9.5	1.5	10.5	ns
t_{PLH}	Propagation Delay I_n to $\overline{Z}_n$	5.0	1.5	4.5	8.0	1.0	8.5	ns
t_{PHL}	Propagation Delay I_n to $\overline{Z}_n$	5.0	1.5	4.0	6.5	1.0	7.5	ns

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

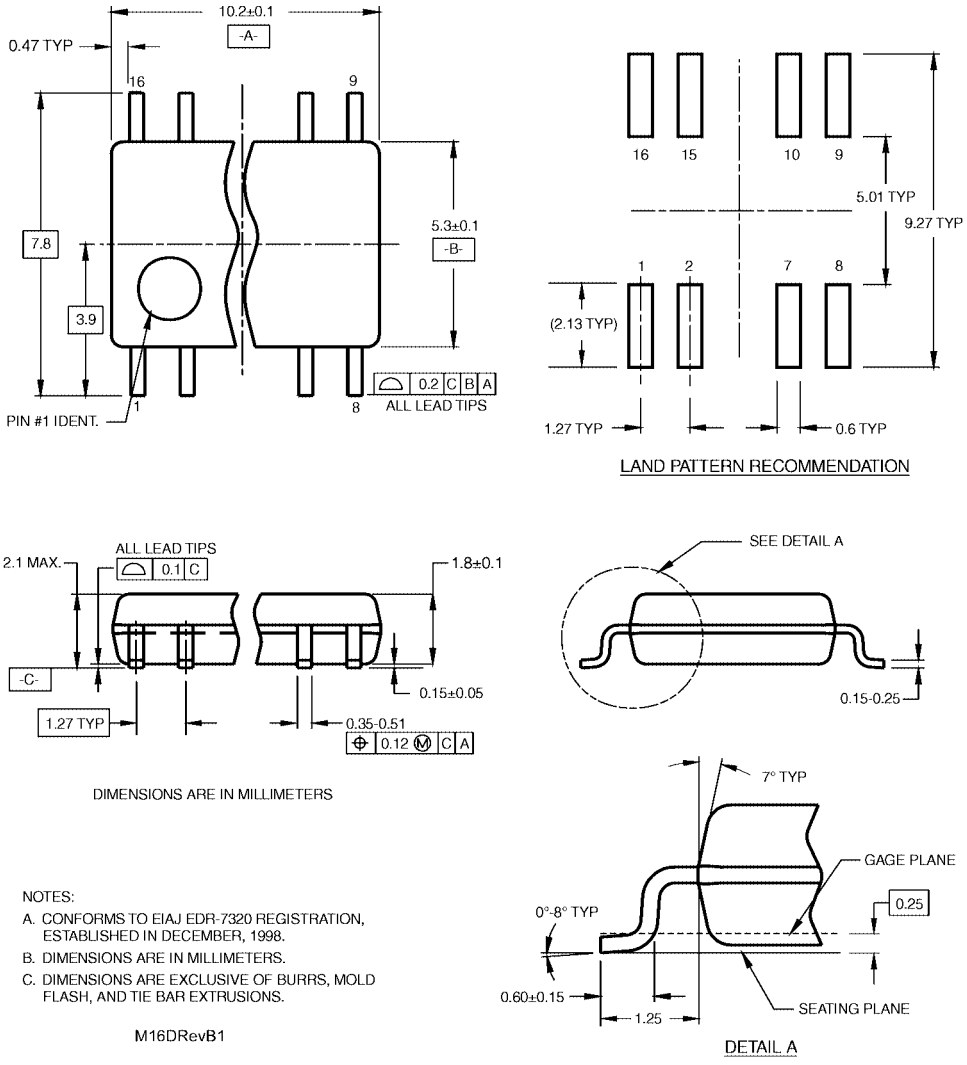
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	45.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16- Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

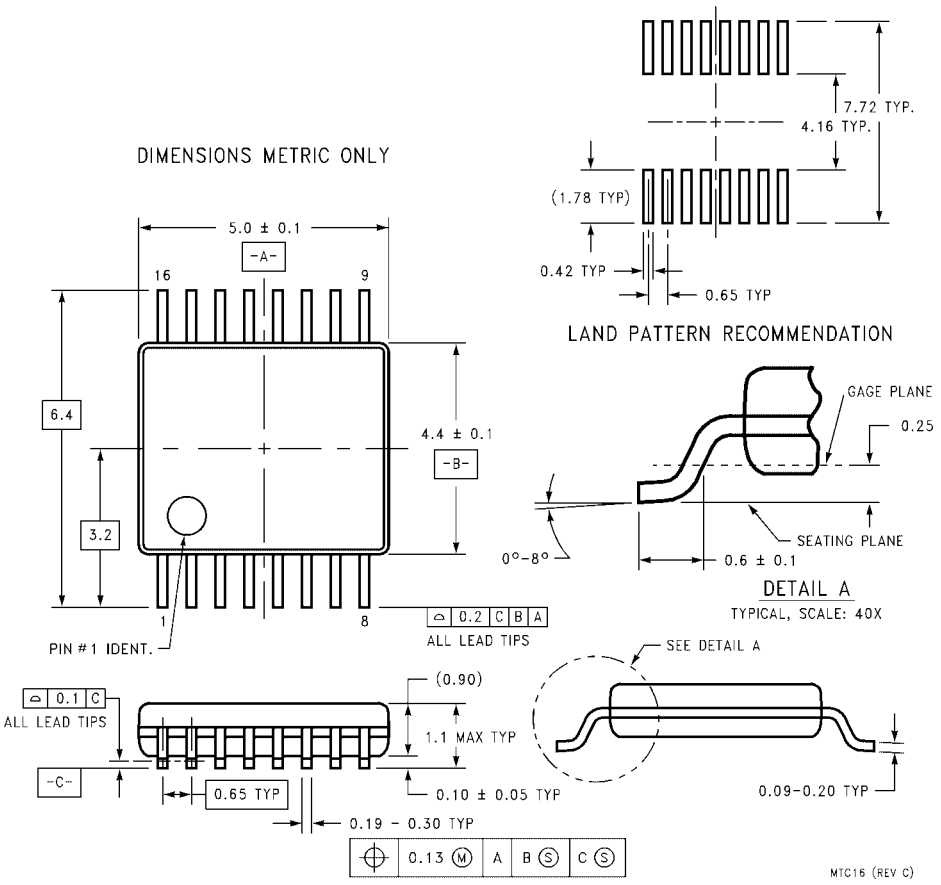
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

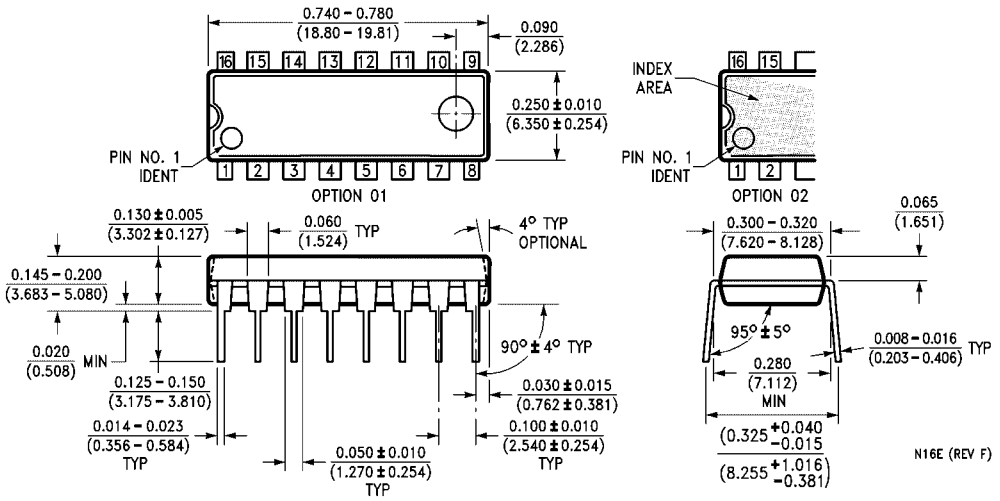
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16- Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16240
16-Bit Inverting Buffer/Line Driver with 3-STATE Outputs

General Description

The ACT16240 contains sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

Features

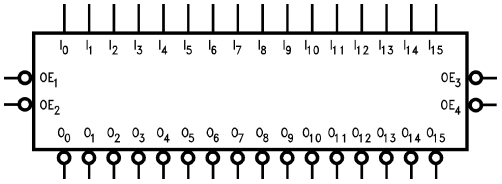
- Separate control logic for each byte
- 16-bit version of the ACT240
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

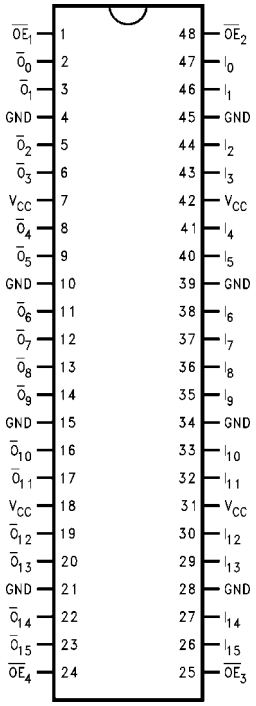
Order Number	Package Number	Package Description
74ACT16240SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

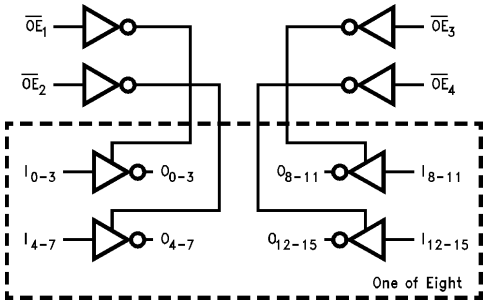
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The ACT16240 contains sixteen inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independently of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin	± 50 mA
Junction Temperature	+140°C
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

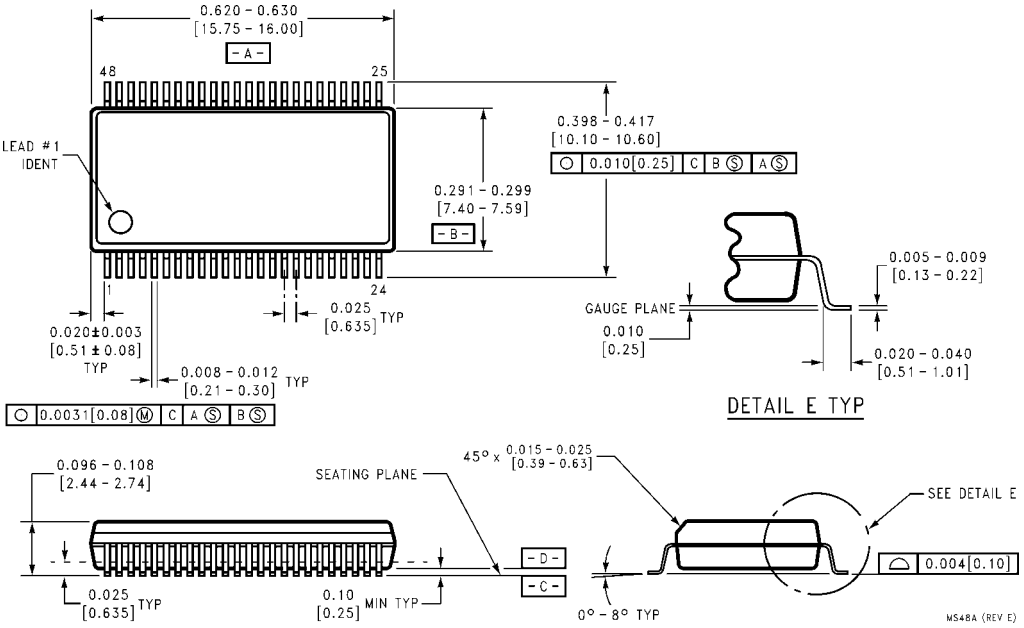
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.7	4.8	7.3	2.7	7.8	ns
t_{PHL}	Data to Output		3.0	5.1	7.3	3.0	7.8	
t_{PZH}	Output Enable Time	5.0	2.5	4.5	7.4	2.5	7.9	ns
t_{PZL}			2.7	4.7	7.5	2.7	8.0	
t_{PHZ}	Output Disable Time	5.0	2.3	5.0	7.9	2.3	8.2	ns
t_{PLZ}			2.0	4.6	7.4	2.0	7.9	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

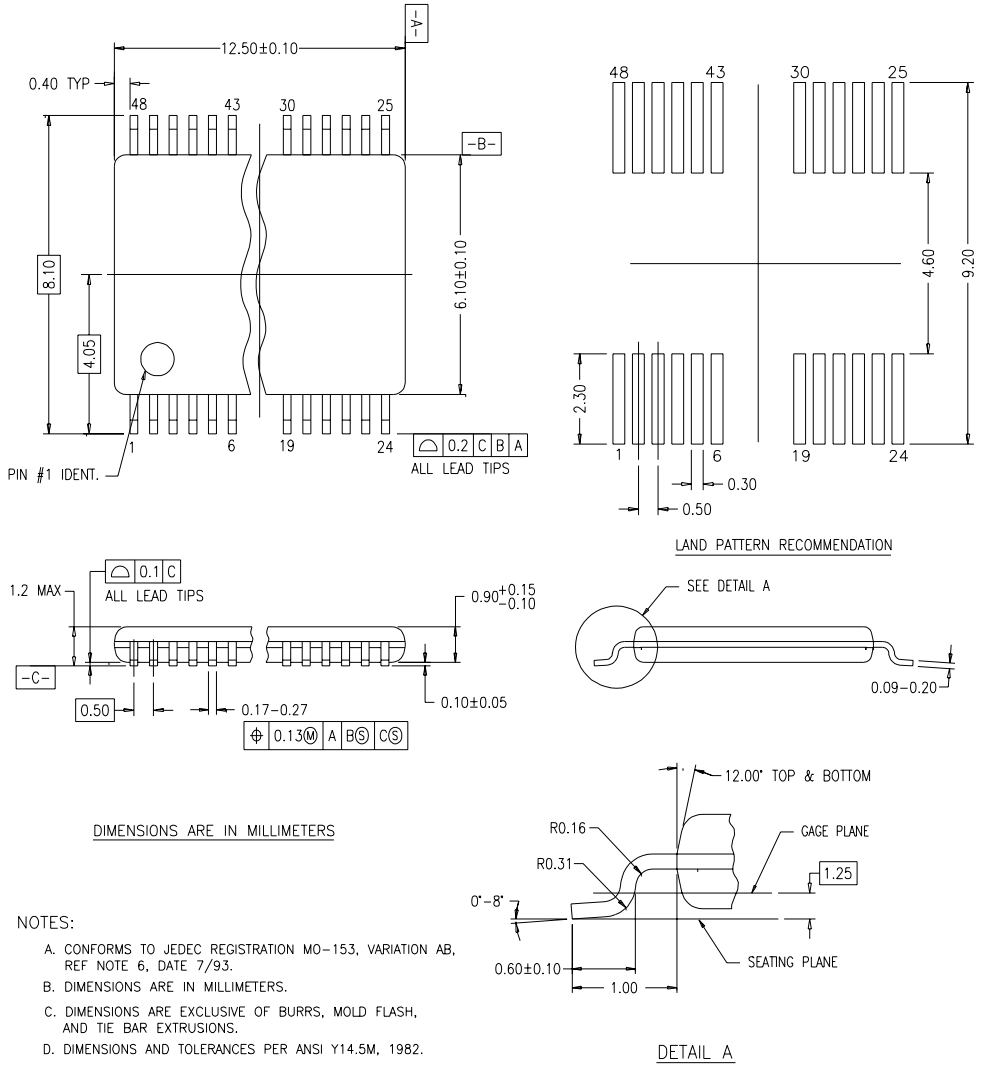
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Think Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16244
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACT16244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

Features

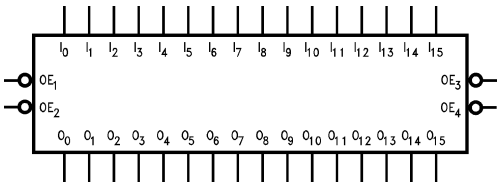
- Separate control logic for each byte and nibble
- 16-bit version of the ACT244
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

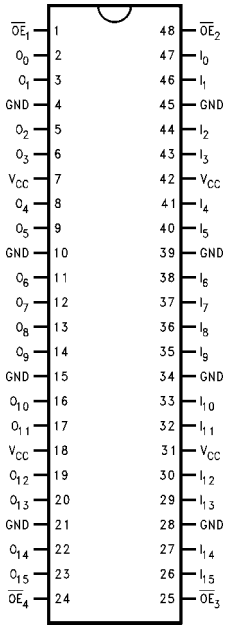
Order Number	Package Number	Package Description
74ACT16244SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT16244 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

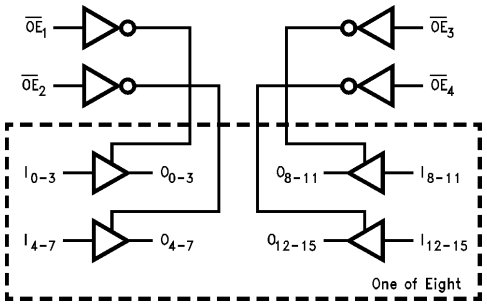
Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	±50 mA
Junction Temperature	+140°C
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
		5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
		5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OH} = 24 mA
		5.5		0.36	0.44		I_{OH} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH}
							V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

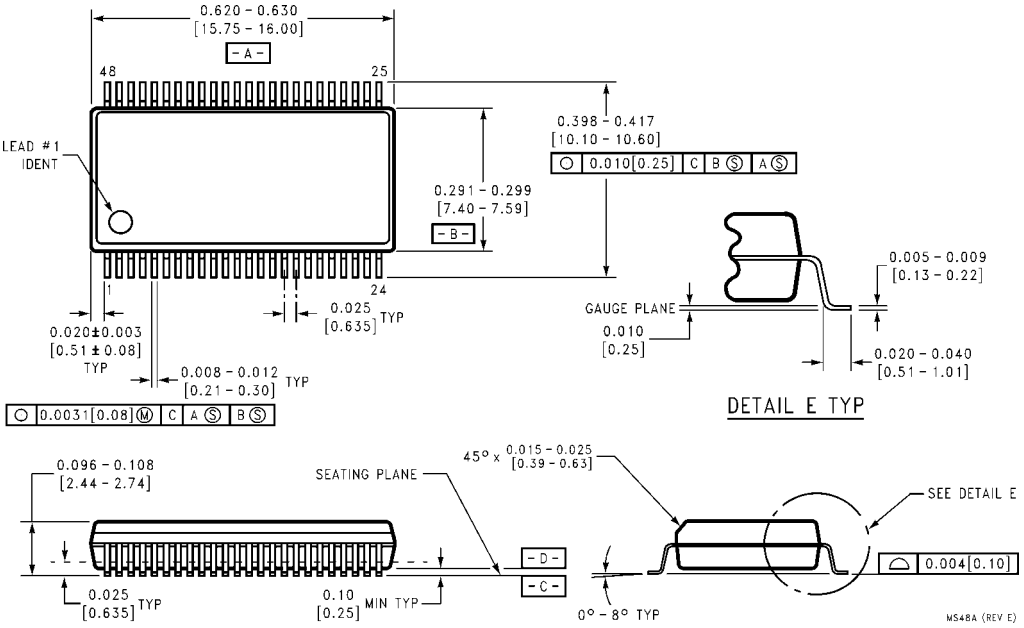
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	5.0	3.0	5.2	7.3	3.0	7.8	ns
t_{PHL}	Delay A_n, B_n to B_n, A_n		2.5	4.8	6.8	2.5	7.3	
t_{PZH}	Output Enable	5.0	2.5	5.0	7.4	2.5	7.9	ns
t_{PZL}	Time		2.7	4.6	7.5	2.7	8.0	
t_{PHZ}	Output Disable	5.0	2.3	5.0	7.9	2.3	8.2	ns
t_{PLZ}	Time		2.0	4.6	7.4	2.0	7.9	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

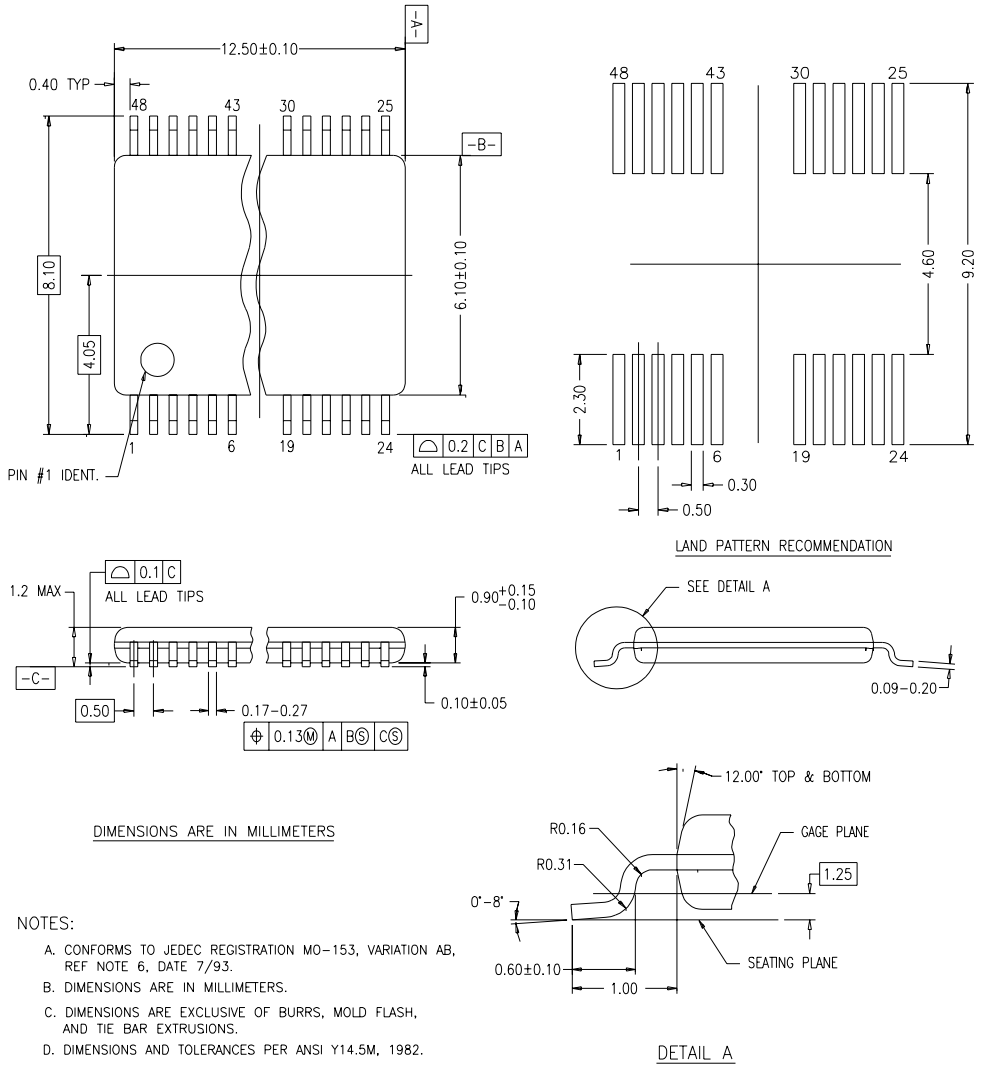
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16245
16-Bit Transceiver with 3-STATE Outputs

General Description

The ACT16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

Features

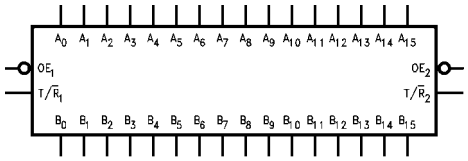
- Bidirectional non-inverting buffers
- Separate control logic for each byte
- 16-bit version of the ACT245
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74ACT16245SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

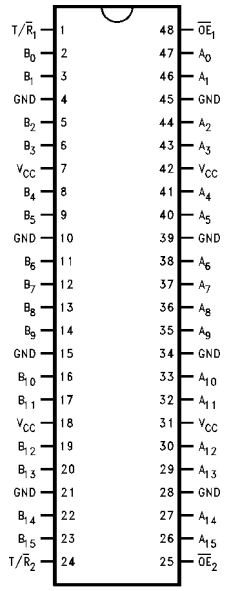
Logic Symbol



Pin Description

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs/Outputs
B_0–B_{15}	Side B Outputs/Inputs

Connection Diagram



FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the $T/\overline{R}$ input is HIGH, then Bus A data is transmitted to Bus B. When the $T/\overline{R}$ input is LOW, Bus B data is transmitted to Bus A. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

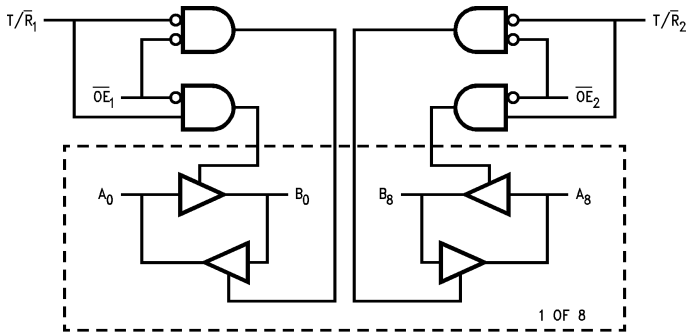
Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH-Z State on A_0–A_7, B_0–B_7

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH-Z State on A_8–A_{15}, B_8–B_{15}

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin	± 50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to+85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

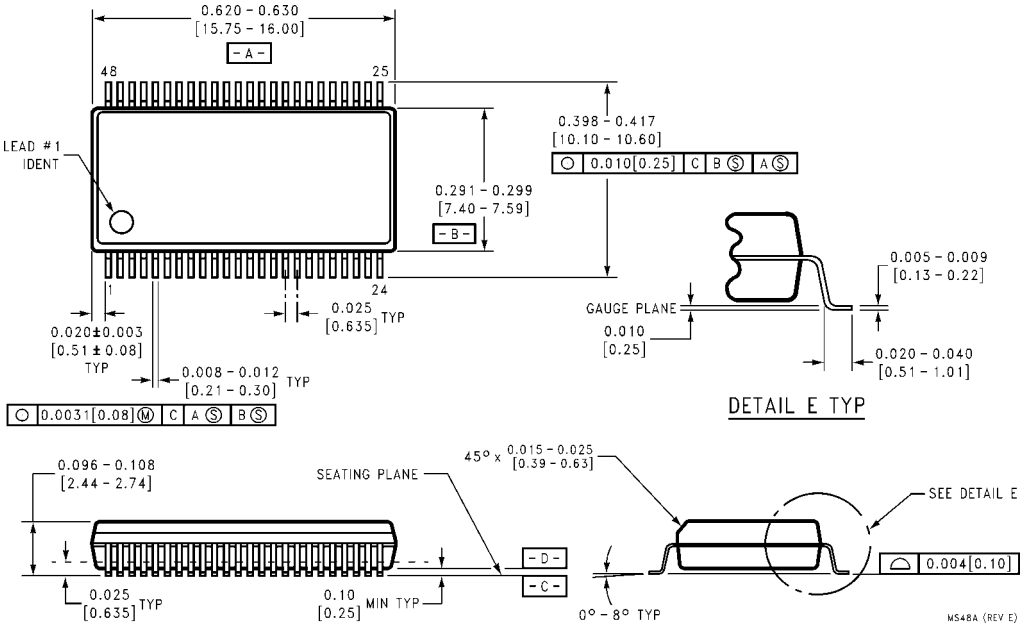
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation	5.0	3.2	5.7	8.4	3.2	9.0	ns
t_{PHL}	Delay A_n, B_n to B_n, A_n		2.6	5.1	7.9	2.6	8.4	
t_{PZH}	Output Enable	5.0	3.7	6.4	9.4	2.7	10.0	ns
t_{PZL}	Time		4.1	7.4	10.5	3.4	11.6	
t_{PHZ}	Output Disable	5.0	2.2	5.4	8.7	2.2	9.3	ns
t_{PLZ}	Time		2.0	5.2	8.2	2.0	8.8	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

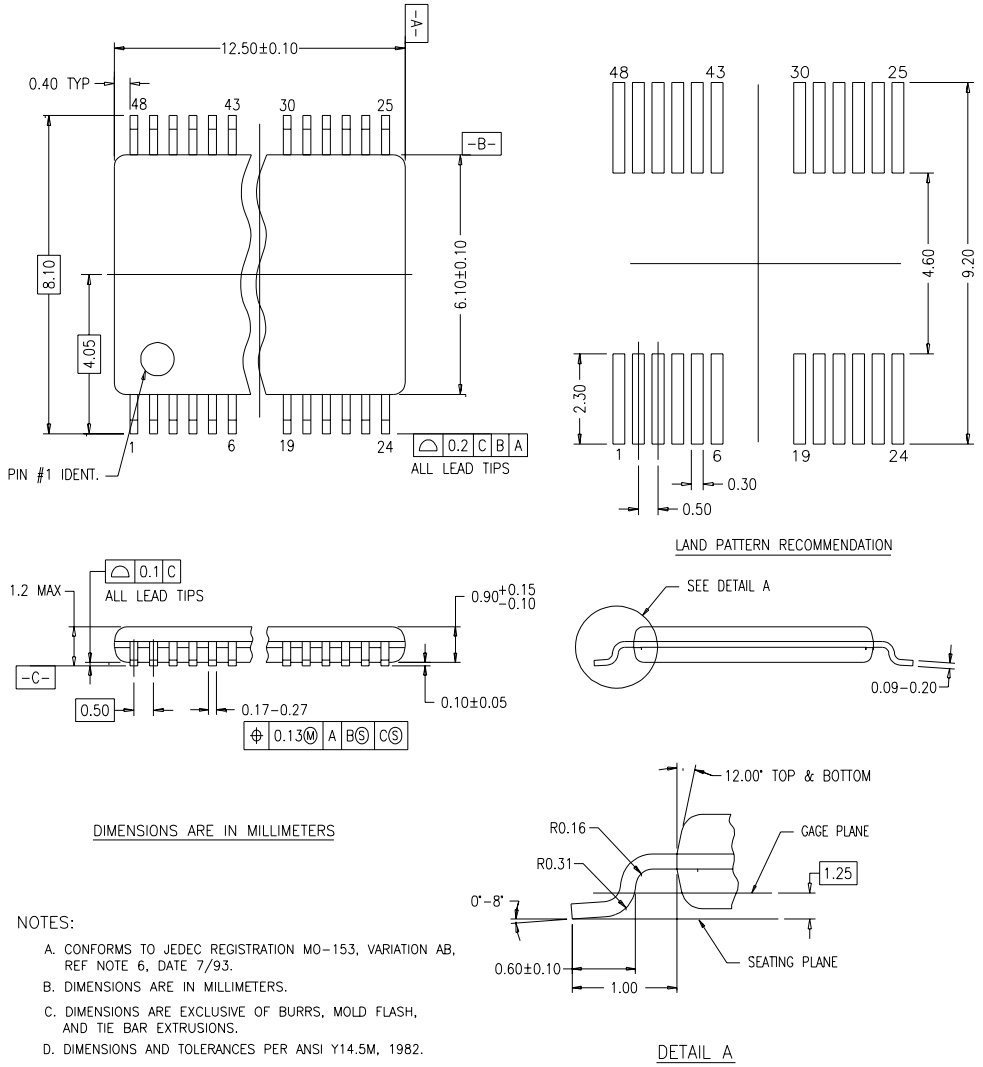
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	25	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16373
16-Bit Transparent Latch with 3-STATE Outputs

General Description

The ACT16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is low, the data that meets the setup time is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the outputs are in high Z state.

Features

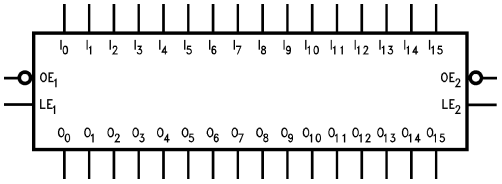
- Separate control logic for each byte
- 16-bit version of the ACT373
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

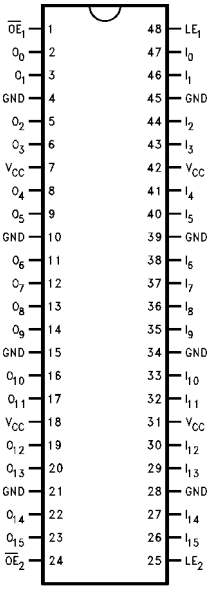
Order Number	Package Number	Package Description
74ACT16373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active Low)
LE_n	Latch Enable Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT16373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the D_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change states each time its D input changes. When LE_n is LOW, the latches store information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

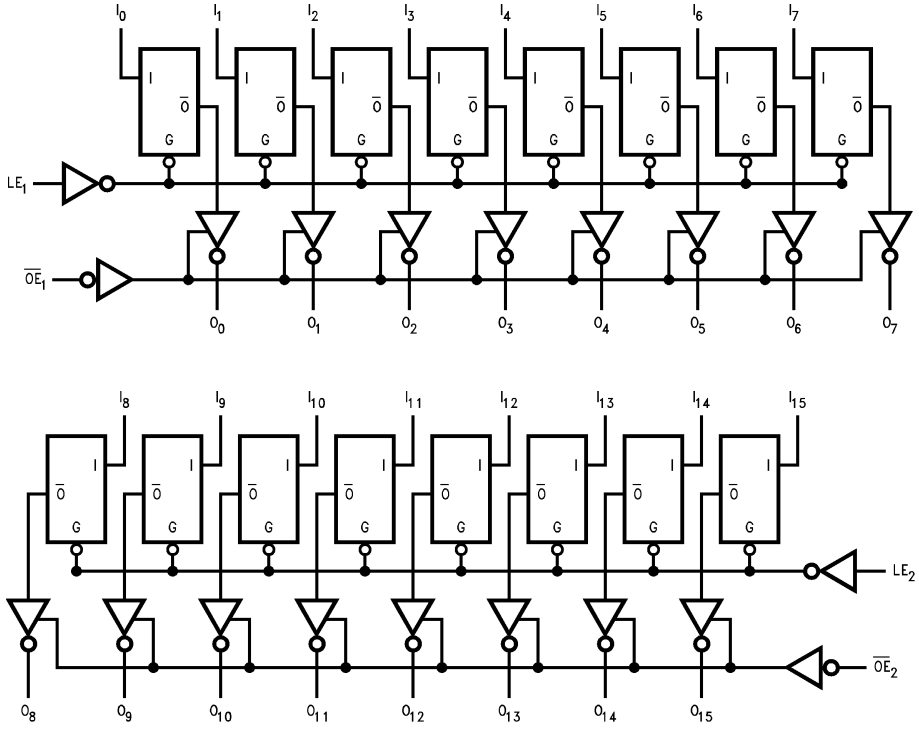
Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	(Previous)

Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	(Previous)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
Previous = previous output prior to HIGH-to-LOW transition of LE

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	+50 mA
DC V_{CC} or Ground Current per Output Pin	+50 mA
Junction Temperature	+140°C
Storage Temperature	−65°C to+150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$) V_{IN} from 0.8V to 2.0V V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = -24$ mA
		5.5		4.86	4.76		$I_{OH} = -24$ mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}$, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	$V_I = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	$V_{IN} = V_{CC}$ or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}					−75	mA	$V_{OHD} = 3.85V$ Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	3.1	5.3	7.9	3.1	8.4	ns
t_{PHL}	D_n to O_n		2.6	4.6	7.3	2.6	7.8	
t_{PLH}	Propagation Delay	5.0	3.1	5.4	7.9	3.2	8.4	ns
t_{PHL}	LE to O_n		2.8	4.9	7.3	2.8	7.8	
t_{PZH}	Output Enable	5.0	2.5	4.7	7.4	2.5	7.9	ns
t_{PZL}	Delay		2.7	4.8	7.5	2.7	8.0	
t_{PHZ}	Output Disable	5.0	2.1	5.1	7.9	2.1	8.2	ns
t_{PLZ}	Delay		2.0	4.5	7.4	2.0	7.9	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

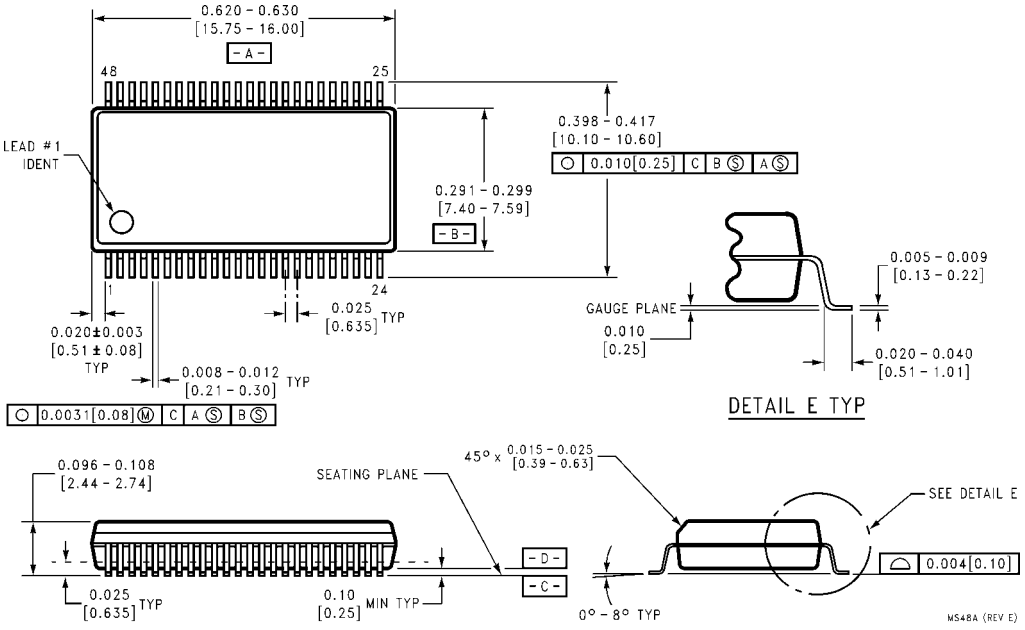
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW, Input to Clock	5.0	3.0	3.0	ns
t_H	Hold time, HIGH or LOW, Input to Clock	5.0	1.5	1.5	ns
t_W	CS Pulse Width, HIGH or LOW	5.0	4.0	4.0	ns

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

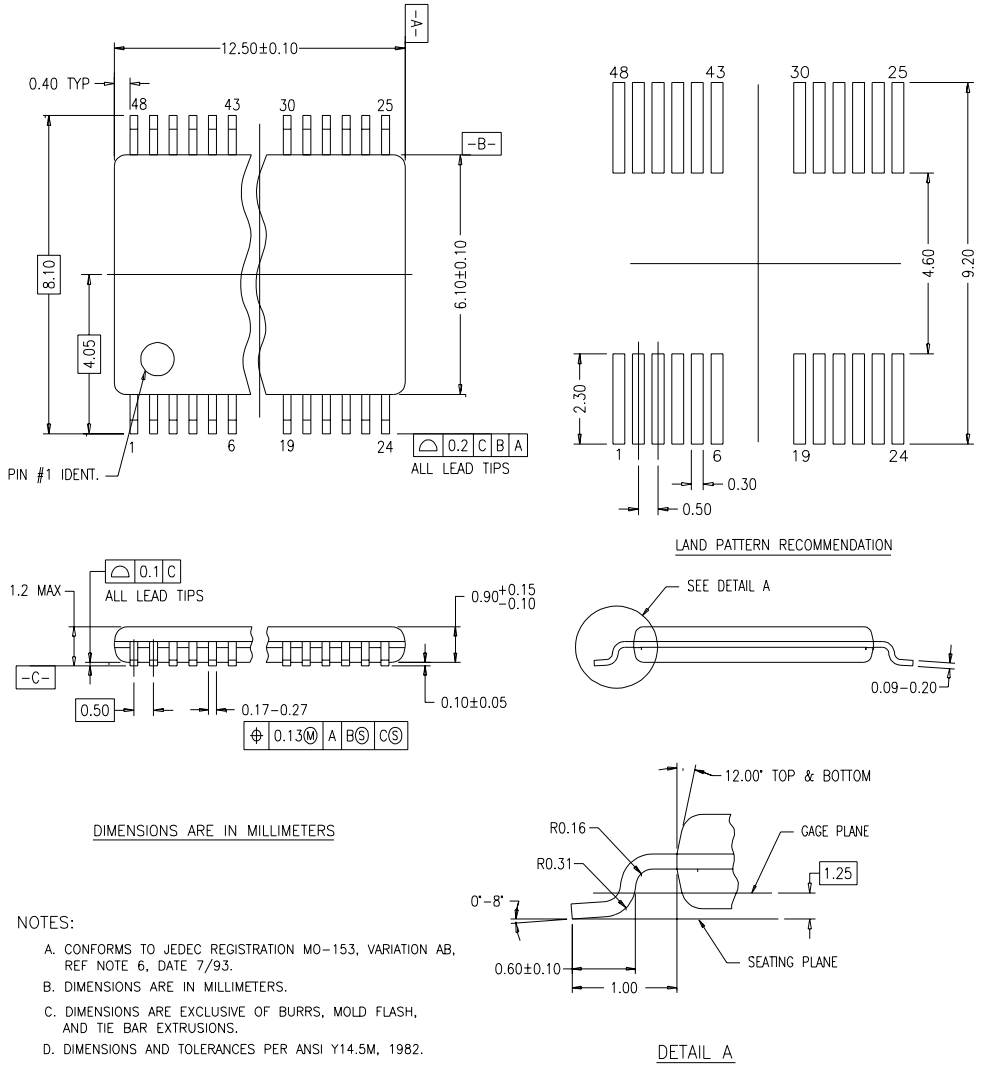
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16374
16-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACT16374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and Output Enable (OE) are common to each byte and can be shorted together for full 16-bit operation.

Features

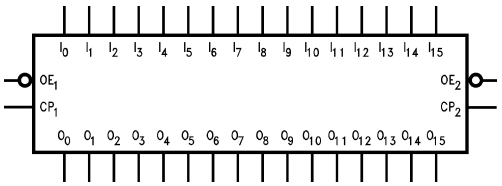
- Buffered Positive edge-triggered clock
- Separate control logic for each byte
- 16-bit version of the ACT374
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

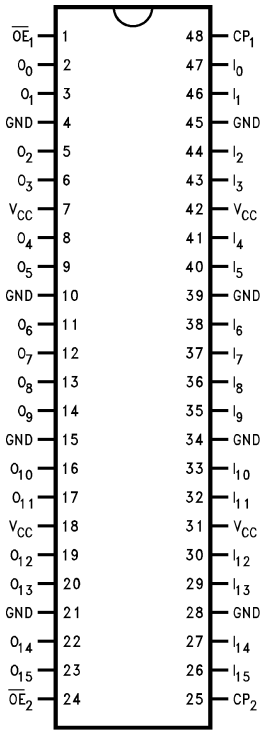
Order Number	Package Number	Package Description
74ACT16374SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT16374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each byte has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operation of the OE_n input does not affect the state of the flip-flops.

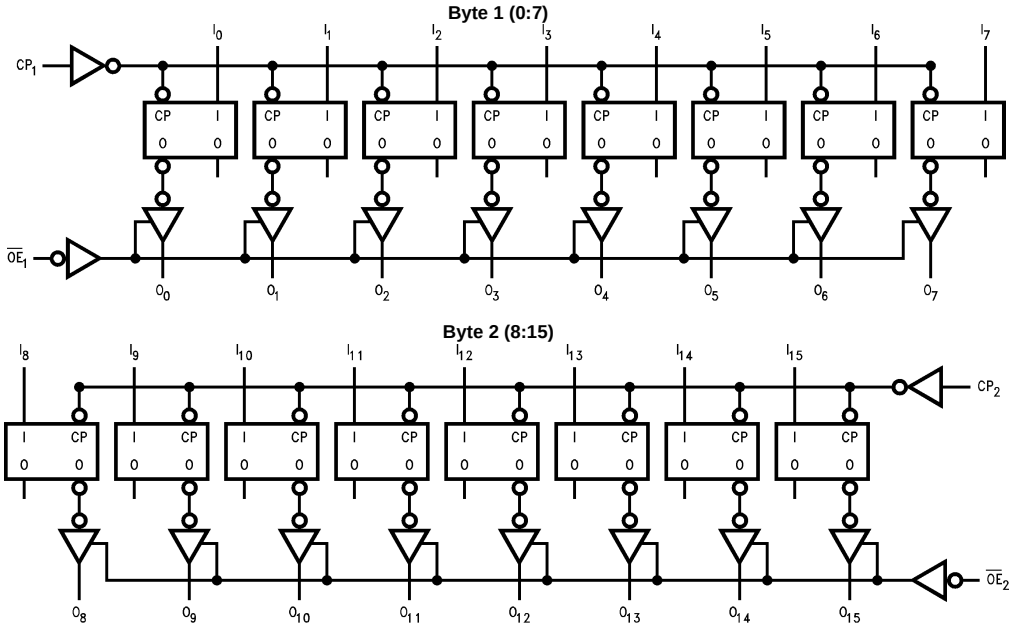
Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
⌐	L	H	H
⌐	L	L	L
L	L	X	(Previous)
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
⌐	L	H	H
⌐	L	L	L
L	L	X	(Previous)
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X= Immaterial
Z = HIGH Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	± 50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	71			67		MHz
t_{PLH}	Propagation Delay	5.0	3.1	5.3	7.9	3.1	8.4	ns
t_{PHL}	CP to O_n		3.0	5.1	7.3	3.0	7.8	
t_{PZH}	Output Enable Time	5.0	2.5	4.7	7.4	2.5	7.9	ns
t_{PZL}			3.0	5.4	8.0	2.0	8.5	
t_{PHZ}	Output Disable Time	5.0	2.1	5.1	7.9	2.1	8.2	ns
t_{PLZ}			2.0	4.8	7.4	2.0	7.9	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

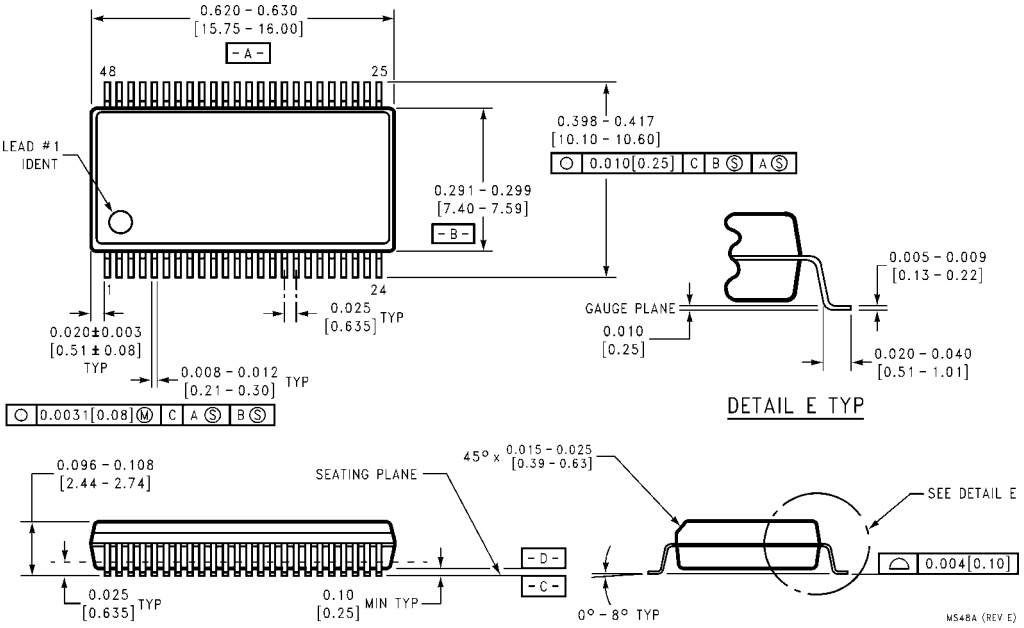
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Limits		
t_S	Setup Time, HIGH or LOW, Input to Clock	5.0	0.7	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW, Input to Clock	5.0	0.8	1.0	1.0	ns
t_W	CP Pulse Width, HIGH or LOW	5.0	1.5	5.0	5.0	ns

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

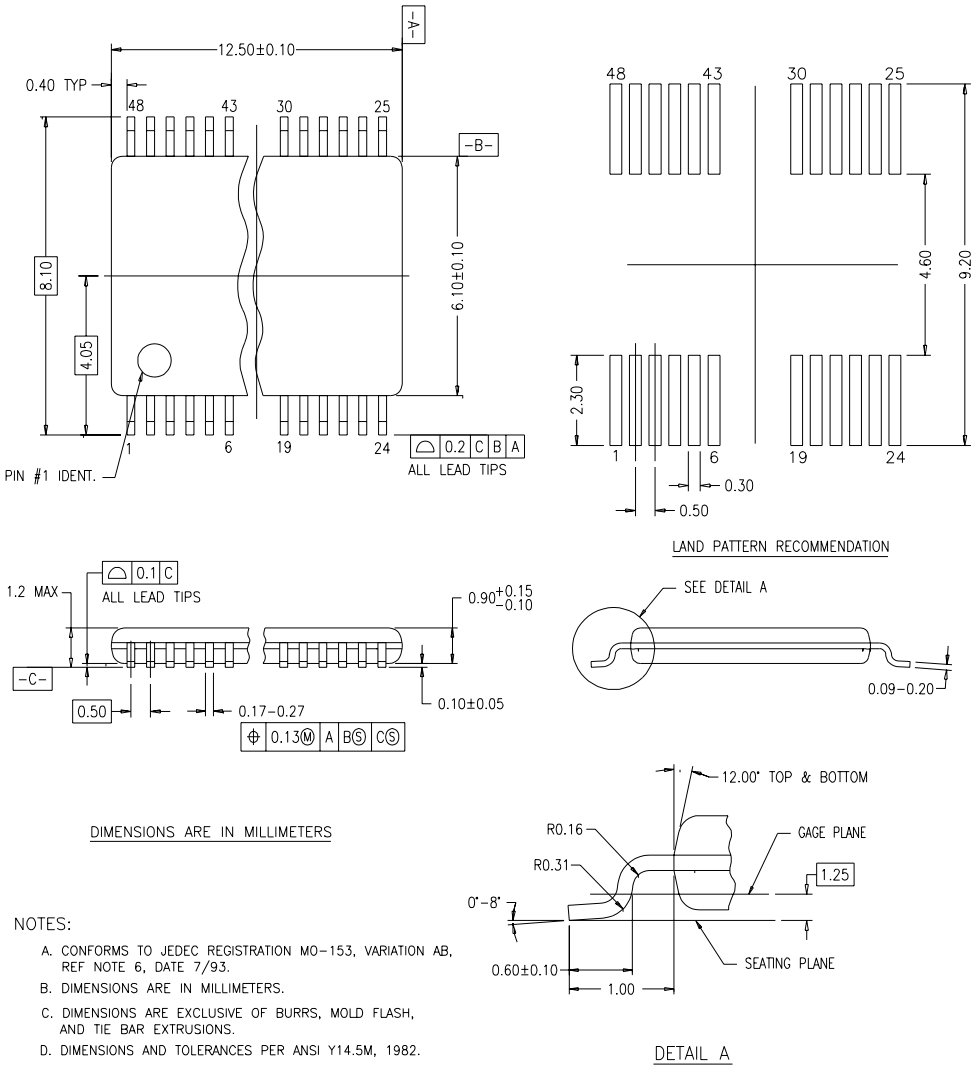
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16540
16-Bit Inverting Buffer/Line Driver with 3-STATE Outputs

General Description

The ACT16540 contains sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

Features

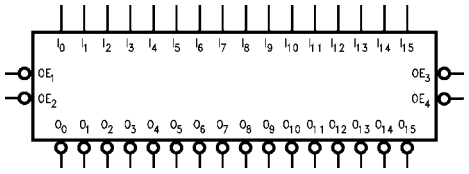
- Separate control logic for each byte
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

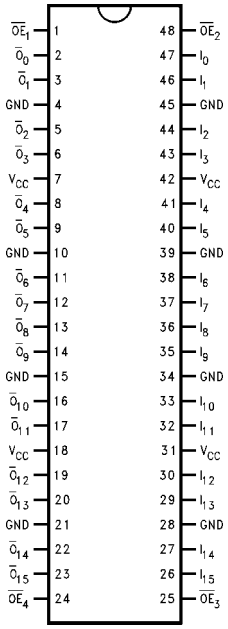
Order Number	Package Number	Package Description
74ACT16540SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16540MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT16540 contains sixteen inverting buffers with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

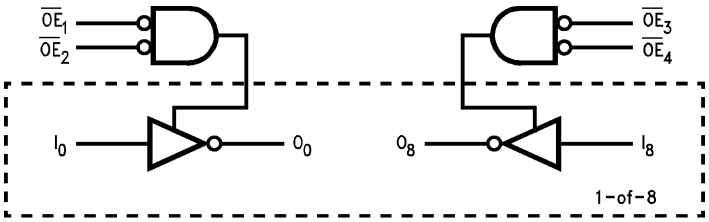
Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_7	$\overline{O}_0$–$\overline{O}_7$
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

Inputs			Outputs
$\overline{OE}_3$	$\overline{OE}_4$	I_8–I_{15}	$\overline{O}_8$–$\overline{O}_{15}$
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin	± 50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

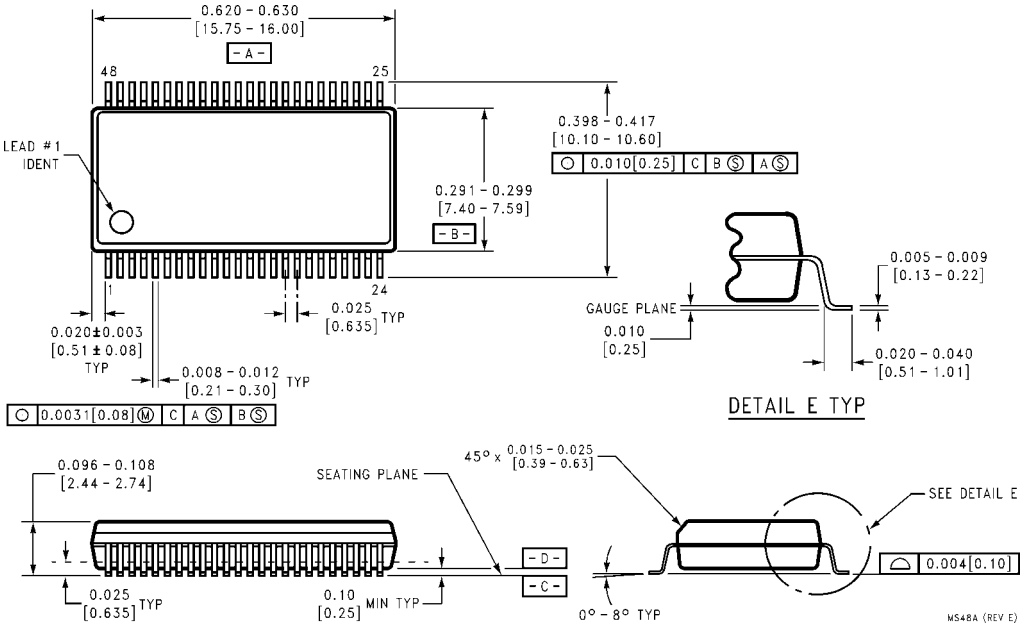
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.7	4.9	7.3	2.7	7.8	ns
t_{PHL}	Data to Output		3.0	5.1	7.3	3.0	7.8	
t_{PZH}	Output Enable	5.0	2.5	4.8	7.4	2.5	7.9	ns
t_{PZL}	Time		2.7	5.3	8.0	2.7	8.5	
t_{PHZ}	Output Disable	5.0	2.5	5.4	8.3	2.5	8.7	ns
t_{PLZ}	Time		2.3	5.0	7.4	2.3	7.9	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

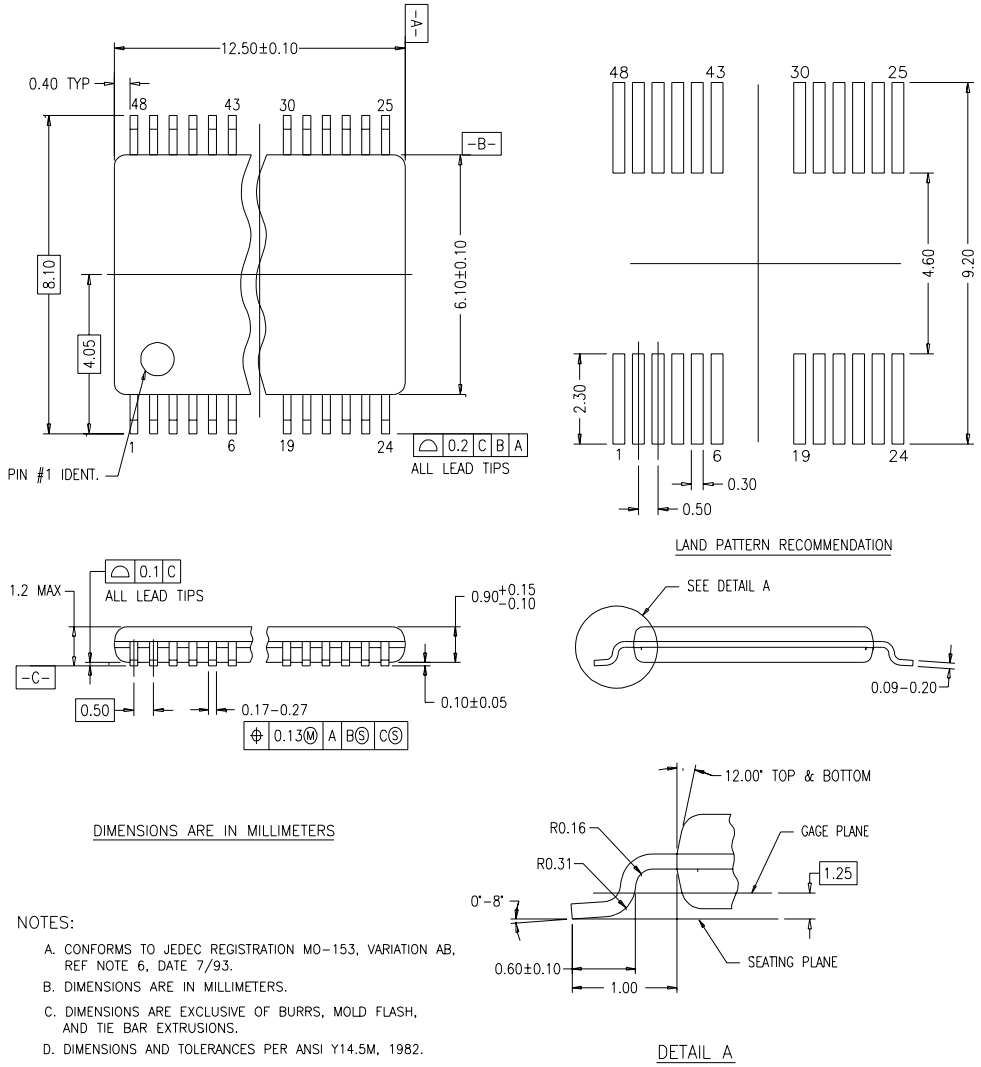
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16541
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACT16541 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

Features

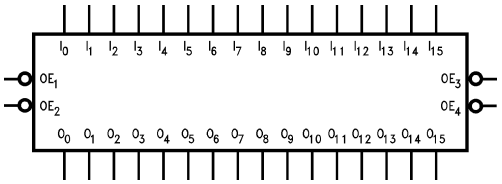
- Separate control logic for each byte
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

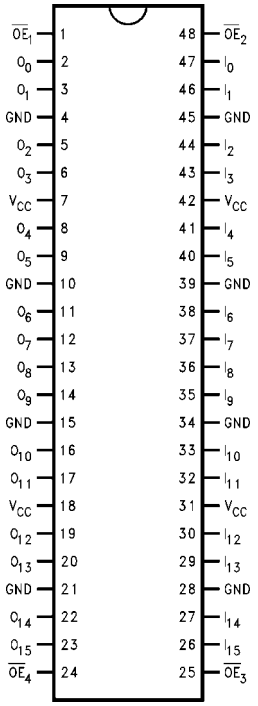
Order Number	Package Number	Package Description
74ACT16541SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16541MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation

Functional Description

The ACT16541 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

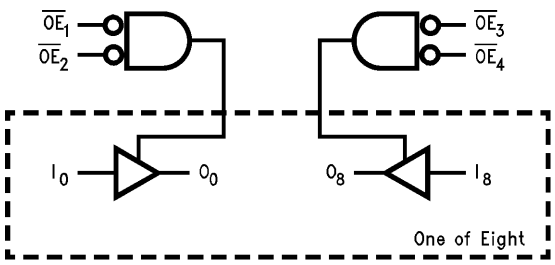
Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_7	O_0–O_7
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

Inputs			Outputs
$\overline{OE}_3$	$\overline{OE}_4$	I_8–I_{15}	O_8–O_{15}
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

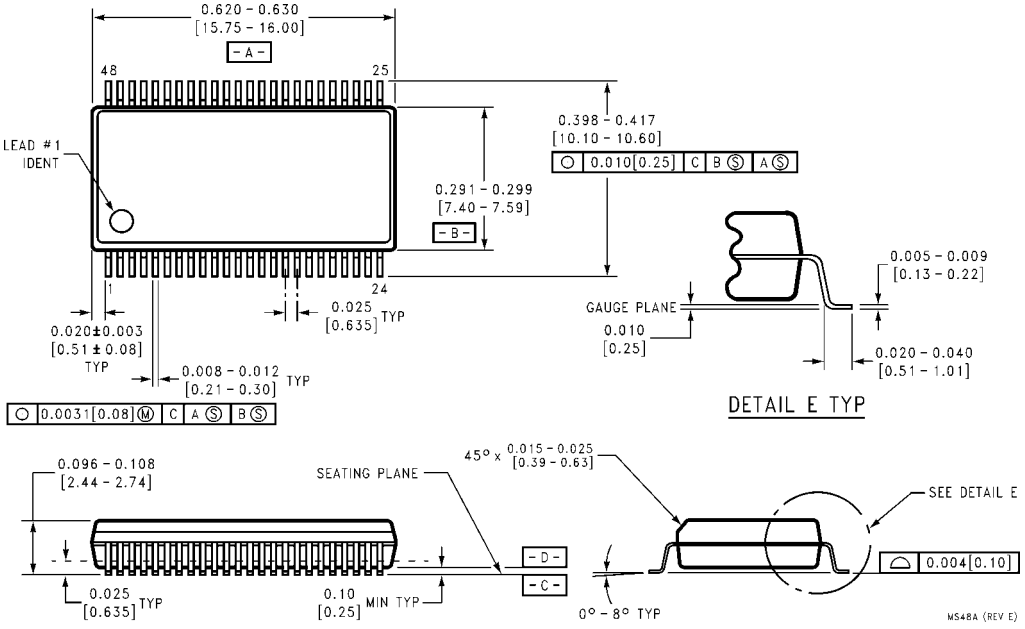
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	3.0	5.2	7.3	3.0	7.8	ns
t_{PHL}	Data to Output		2.5	4.8	7.3	2.5	7.8	
t_{PZH}	Output Enable Time	5.0	2.6	5.0	7.4	2.6	7.9	ns
t_{PZL}			2.7	5.4	8.0	2.7	8.5	
t_{PHZ}	Output Disable Time	5.0	2.7	5.6	8.3	2.7	8.7	ns
t_{PLZ}			2.4	5.2	7.9	2.4	8.4	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

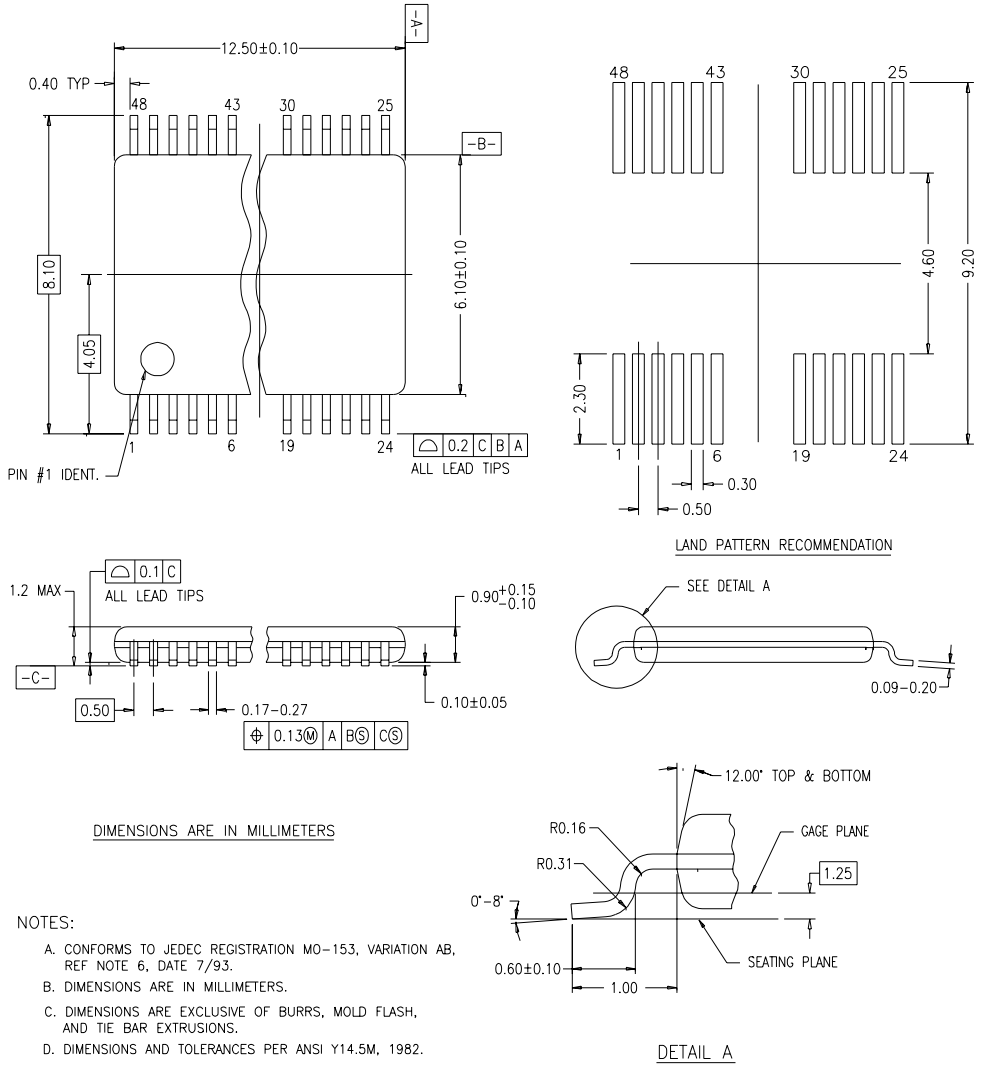
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	30	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16543
16-Bit Registered Transceiver with 3-STATE Outputs

General Description

The ACT16543 contains sixteen non-inverting transceivers containing two sets of D-type registers for temporary storage of data flowing in either direction. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

Features

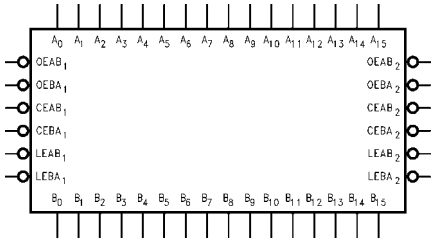
- Independent registers for A and B buses
- Separate controls for data flow in each direction
- Back-to-back registers for storage
  Multiplexed real-time and stored data transfers
- Separate control logic for each byte
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

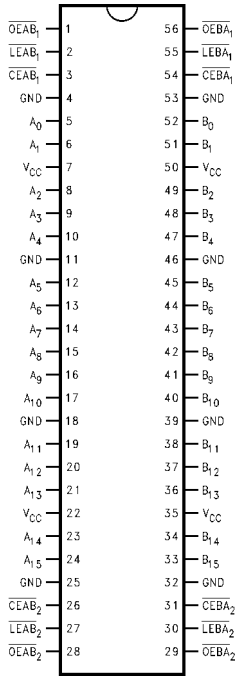
Order Number	Package Number	Package Description
74ACT16543SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16543MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Descriptions
$\overline{OEAB}_n$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}_n$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}_n$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}_n$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}_n$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}_n$	B-to-A Latch Enable Input (Active LOW)
A_0–A_{15}	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B_0–B_{15}	B-to-A Data Inputs or A-to-B 3-STATE Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT16543 contains sixteen non-inverting transceivers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The following description applies to each byte. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}_n$) input must be LOW in order to enter data from A_0–A_{15} or take data from B_0–B_{15}, as indicated in the Data I/O Control Table. With $\overline{CEAB}_n$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}_n$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}_n$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}_n$ and $\overline{OEAB}_n$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$ inputs.

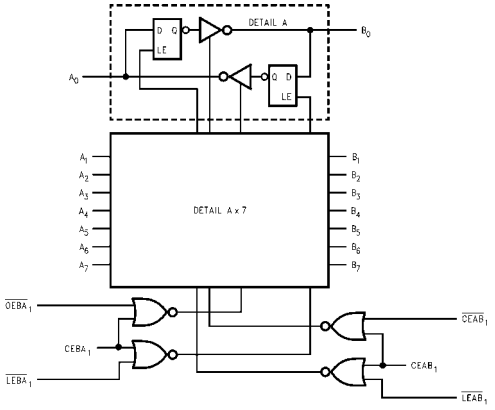
Data I/O Control Table

Inputs			Latch Status (Byte n)	Output Buffers (Byte n)
$\overline{CEAB}_n$	$\overline{LEAB}_n$	$\overline{OEAB}_n$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

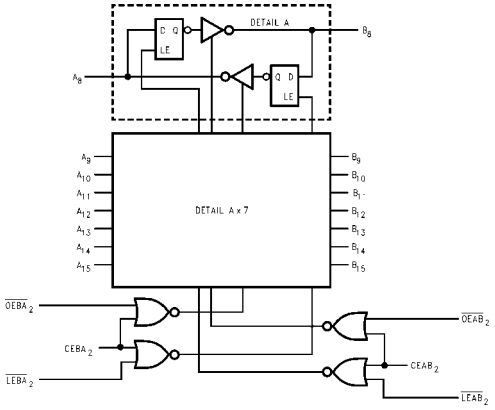
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$

Logic Diagrams

Byte 1 (0:7)



Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW	4.5	0.001	0.1	0.1	V	
	Output Voltage	5.5	0.001	0.1	0.1		I_{OUT} = 50 μA
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZT}	Maximum I/O	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{IN}	Maximum Input	5.5		±0.1	±1.0	μA	V_I = V_{CC},
	Leakage Current						GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent	5.5		8.0	80.0	μA	V_{IN} = V_{CC}
	Supply Current						or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	3.8	5.9	8.3	3.0	9.0	ns
t_{PHL}	Transparent Mode		3.5	5.5	7.9	2.6	8.5	
	A_n to $B_n$or B_n to A_n							
t_{PLH}	Propagation Delay	5.0	4.7	6.9	9.8	3.4	10.8	ns
t_{PHL}	$\overline{LEBA}_n$, $\overline{LEAB}_n$		3.9	6.3	9.0	3.1	9.8	
	to A_n, B_n							
t_{PZH}	Output Enable Time	5.0	4.2	6.3	9.2	3.0	9.9	ns
t_{PZL}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n		4.9	7.3	10.3	3.6	10.3	
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n							
t_{PHZ}	Output Disable Time	5.0	2.8	5.2	8.0	2.1	8.3	ns
t_{PLZ}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n		2.6	5.0	7.6	2.0	8.1	
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n							

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

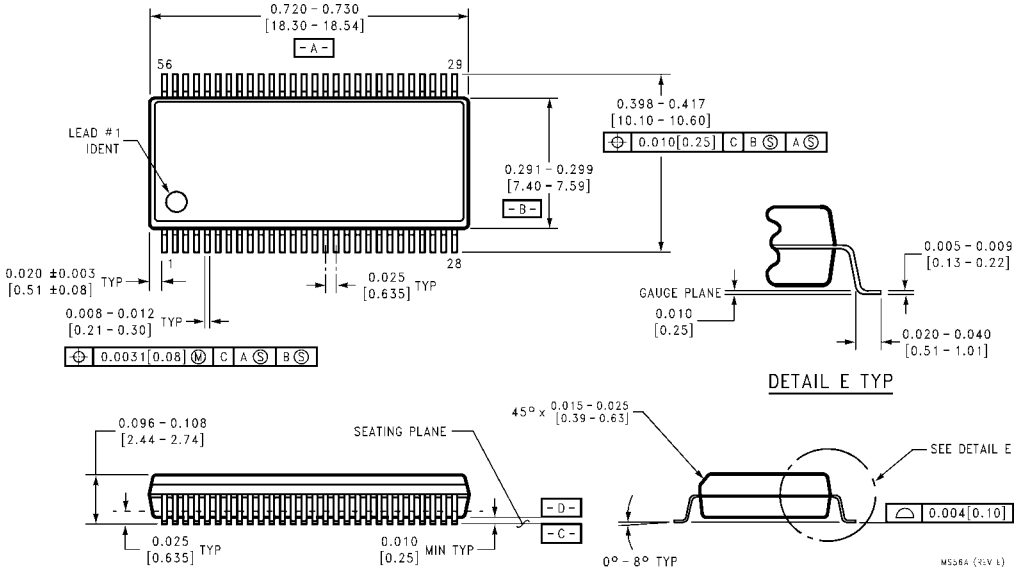
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	5.0	3.0	3.0	ns
	A_n or B_n to $\overline{LEBA}_n$ or $\overline{LEAB}_n$				
t_H	Hold Time, HIGH or LOW	5.0	1.5	1.5	ns
	A_n or B_n to $\overline{LEBA}_n$ or $\overline{LEAB}_n$				
t_W	Latch Enable, B to A	5.0	4.0	4.0	ns
	Pulse Width, LOW				

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

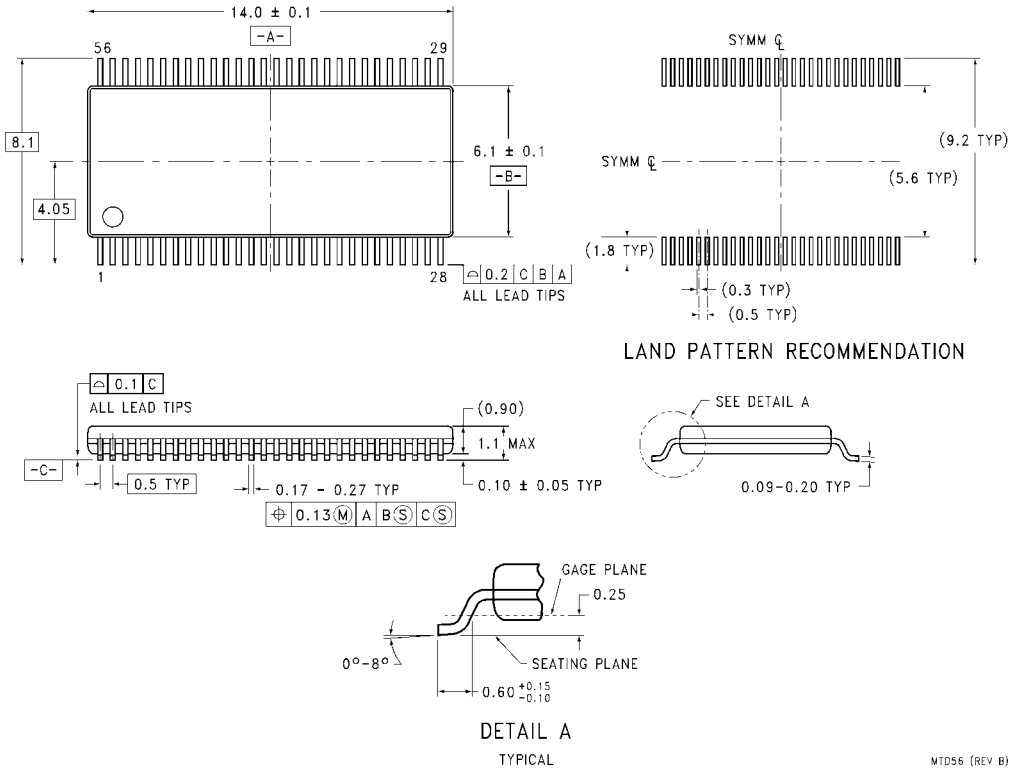
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation.Capacitance	95.0	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (SSOP), JEDEC MO-153, 6.1mm Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT16646
16-Bit Transceiver/Register with 3-STATE Outputs

General Description

The ACT16646 contains sixteen non-inverting bidirectional registered bus transceivers providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition.

Features

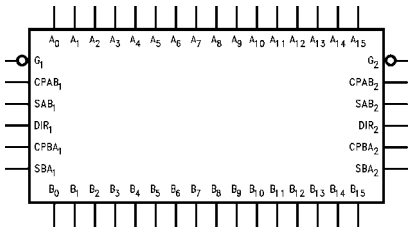
- Independent registers for A and B buses
- Multiplexed real-time and stored data transfers
- Separate control logic for each byte
- 16-bit version of the ACT646
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

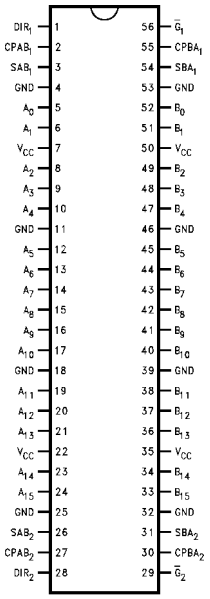
Order Number	Package Number	Package Description
74ACT16646SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16646MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



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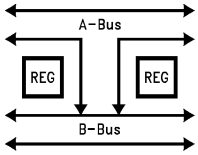
Function Table

Inputs						Data I/O (Note 1)		Output Operation Mode
G_1	DIR_1	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_{0-7}	B_{0-7}	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data Into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data to A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n into B Register and Output to A_n

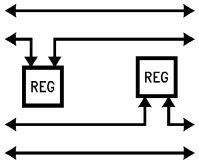
H = HIGH Voltage Level X = Immaterial L = LOW Voltage Level ↑ = LOW-to-HIGH Transition.

Note 1: The data output functions may be enabled or disabled by various signals at the G and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

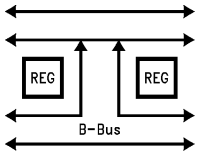
Real Time Transfer A-Bus to B-Bus



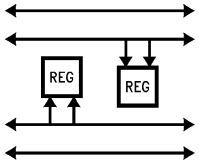
Storage from Bus to Register



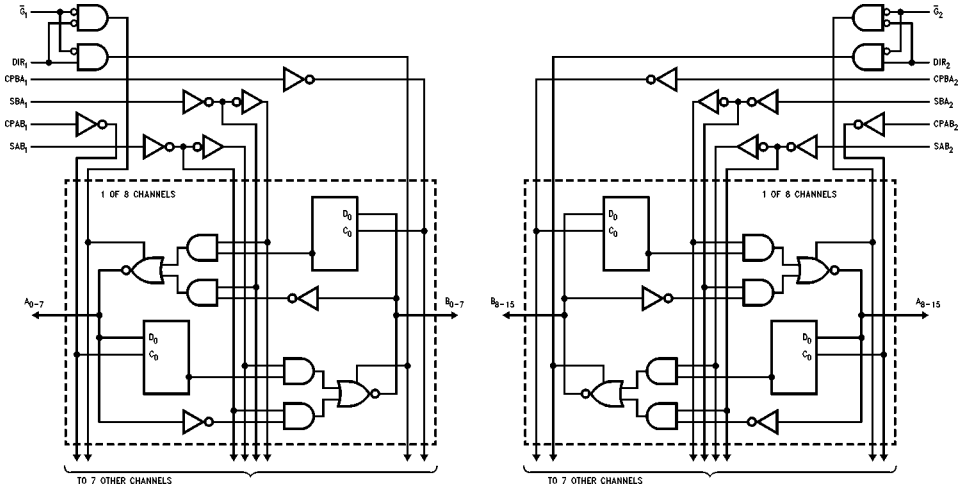
Real Time Transfer B-Bus to A-Bus



Transfer from Register to Bus



Logic Diagram



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.5	±5.0	μA	V_{IN} = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 3: All outputs loaded; thresholds associated with output under test.

Note 4: Maximum test duration 2.0 ms; one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	4.6	6.9	9.4	3.6	10.1	ns
t_{PLH}	Clock to Bus		4.3	6.5	8.9	3.3	9.7	
t_{PHL}	Propagation Delay	5.0	4.0	6.2	8.5	2.9	9.2	ns
t_{PLH}	Bus to Bus		4.1	6.4	8.6	3.2	9.3	
t_{PHL}	Propagation Delay	5.0	4.0	6.4	8.9	3.1	9.6	ns
t_{PLH}	Select to Bus		4.2	6.7	9.5	3.2	10.4	
	(w/An or Bn HIGH or LOW)							
t_{PZL}	Enable Time	5.0	5.3	7.8	10.5	3.8	11.4	ns
t_{PZH}	G to An/Bn		4.6	6.9	9.4	3.3	10.2	
t_{PLZ}	Disable Time	5.0	3.0	5.5	8.1	2.3	8.6	ns
t_{PHZ}	G to An/Bn		3.4	5.7	8.3	2.6	8.6	
t_{PZL}	Enable Time	5.0	5.1	8.2	11.8	4.3	12.7	ns
t_{PZH}	DIR to An/Bn		4.6	7.5	10.8	3.7	11.7	
t_{PLZ}	Disable Time	5.0	2.9	5.8	9.2	2.0	9.8	ns
t_{PHZ}	DIR to An/Bn		3.4	6.1	9.2	2.5	9.7	

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

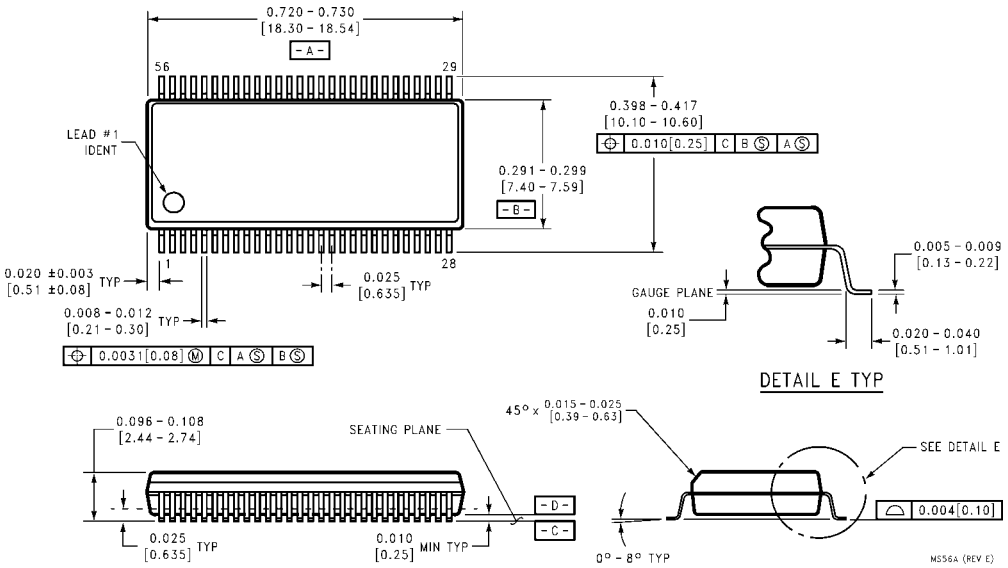
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, H or L Bus to Clock	5.0	3.0	3.0	ns
t_H	Hold Time, H or L Bus to Clock	5.0	1.5	1.5	ns
t_W	Clock Pulse Width H or L	5.0	4.0	4.0	ns

Note 6: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

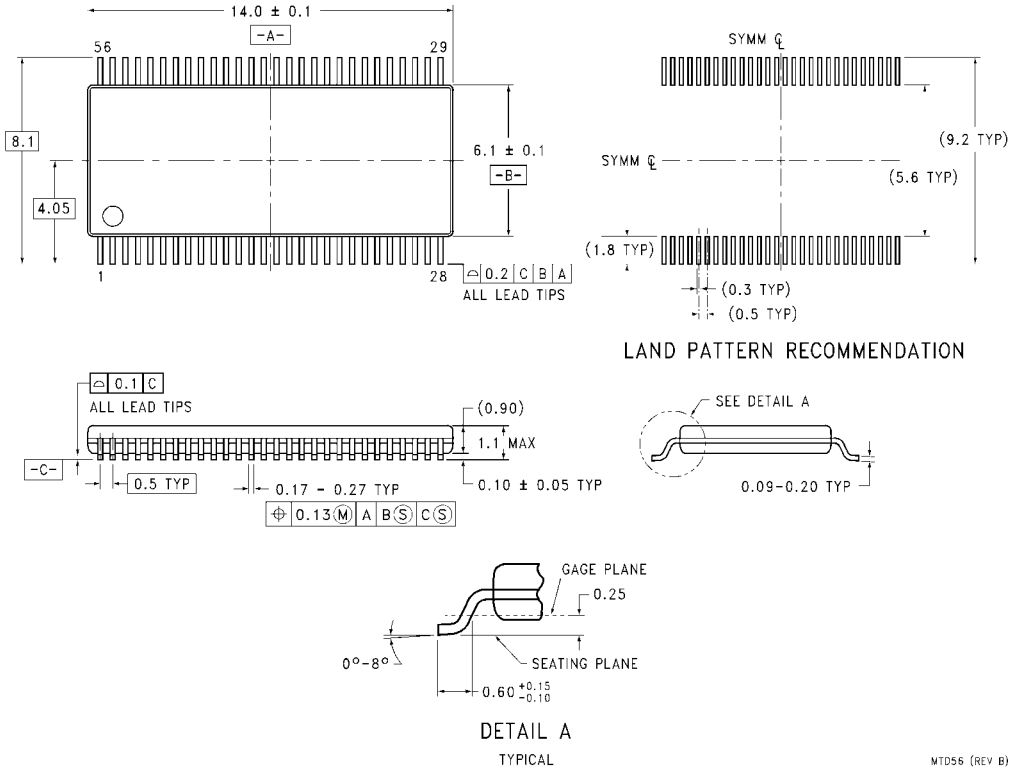
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	95	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT18823
18-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACT18823 contains eighteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock ($\overline{CP}$), Clear ($\overline{CLR}$), Clock Enable ($\overline{EN}$) and Output Enable ($\overline{OE}$) are common to each byte and can be shorted together for full 18-bit operation.

Features

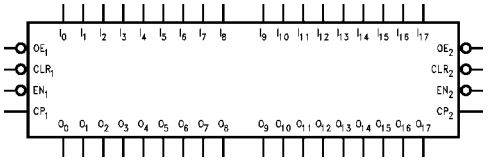
- Broadside pinout allows for easy board layout
- Separate control logic for each byte
- Extra data width for wider address/data paths or buses carrying parity
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

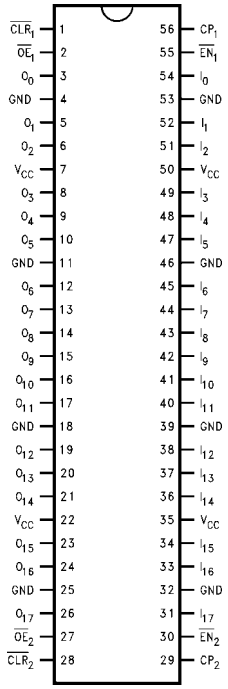
Order Number	Package Number	Package Description
74ACT18823SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT18823MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$\overline{CLR}_n$	Clear (Active LOW)
$\overline{EN}_n$	Clock Enable (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{17}	Inputs
O_0–O_{17}	Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT18823 consists of eighteen D-type edge-triggered flip-flops. These have 3-STATE outputs for bus systems organized with inputs and outputs on opposite sides. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. The buffered clock (CP_n) and buffered Output Enable ($\overline{OE}_n$) are common to all flip-flops within that byte. The flip-flops will store the state of their individual D inputs that meet set-up and hold time requirements on the LOW-to-HIGH CP_n transition. With $\overline{OE}_n$ LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the impedance state. Operation of the $\overline{OE}_n$ input does not affect the state of the flip-flops. In addition to the Clock and Output Enable pins, there are Clear ($\overline{CLR}_n$) and Clock Enable ($\overline{EN}_n$) pins. These devices are ideal for parity bus interfacing in high performance systems.

When $\overline{CLR}_n$ is LOW and $\overline{OE}_n$ is LOW, the outputs are LOW. When $\overline{CLR}_n$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}_n$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}_n$ is HIGH, the outputs do not change state, regardless of the data or clock input transitions.

Function Table

(Note 1)

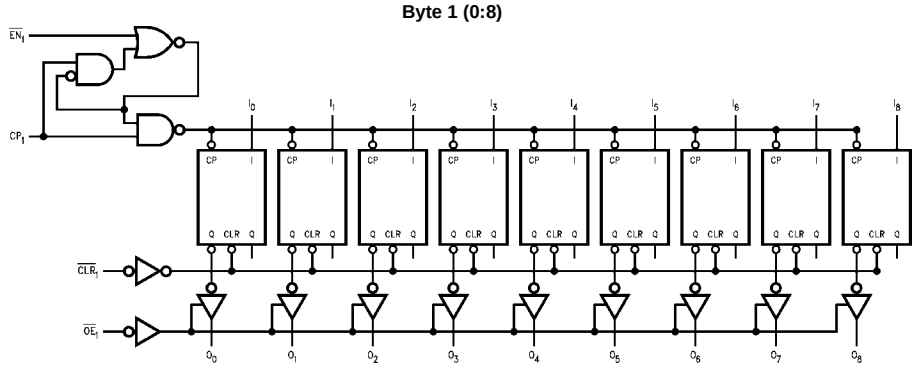
Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	I_n	Q	O_n	
H	X	L	⌐	L	L	Z	High Z
H	X	L	⌐	H	H	Z	High Z
H	L	X	X	X	L	Z	Clear
L	L	X	X	X	L	L	Clear
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	H	L	⌐	L	L	Z	Load
H	H	L	⌐	H	H	Z	Load
L	H	L	⌐	L	L	L	Load
L	H	L	⌐	H	H	H	Load

H= HIGH Voltage Level
L= LOW Voltage Level
X= Immaterial
Z= High Impedance
⌐= LOW-to-HIGH Transition
NC= No Change

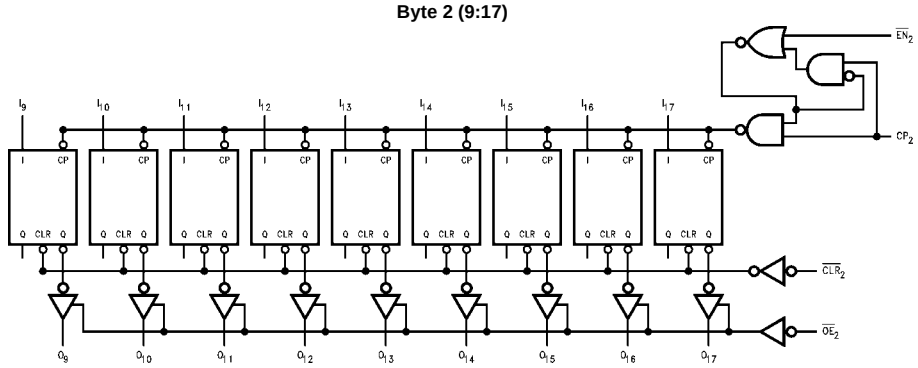
Note 1: The table represents the logic for one byte. The two bytes are independent of each other and function identically.

Logic Diagrams

Byte 1 (0:8)



Byte 2 (9:17)



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
Per Output Pin	± 50 mA
Junction Temperature	
PDIP/SOIC	+140°C
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 3: All outputs loaded; thresholds associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	100		90		MHz
t_{PHL}	Propagation Delay	5.0	2.0	9.0	2.0	9.5	ns
t_{PLH}	CP_n to O_n		2.0	9.0	2.0	9.5	
t_{PHL}	Propagation Delay $\overline{CLR}_n$ to O_n	5.0	2.0	9.0	2.0	9.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	9.0	2.0	10.0	ns
t_{PZH}			2.0	9.0	2.0	10.0	
t_{PLZ}	Output Disable Time	5.0	1.5	7.0	1.5	7.5	ns
t_{PHZ}			1.5	8.0	1.5	8.5	

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

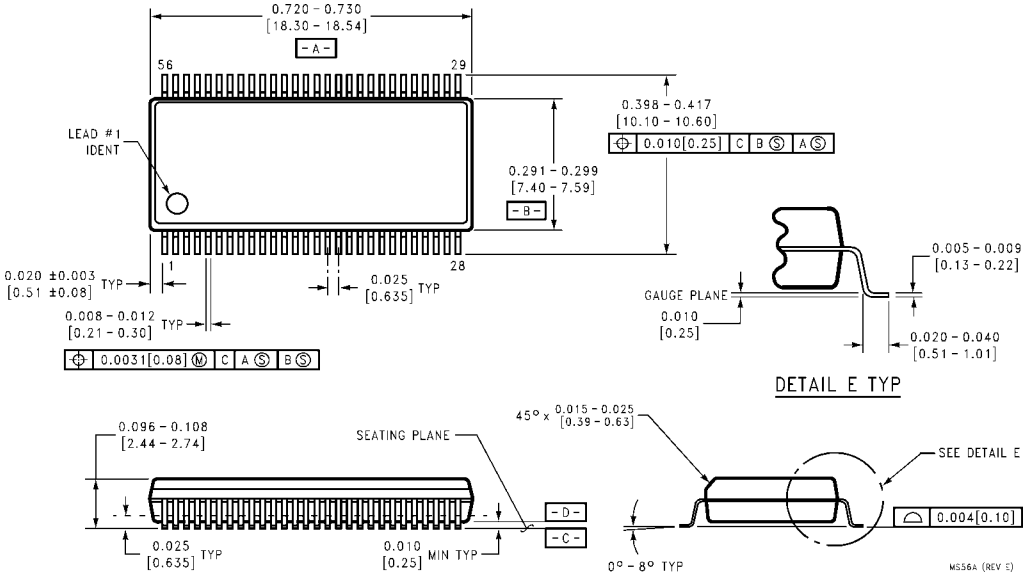
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW, Input to Clock	5.0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW, Input to Clock	5.0	1.5	1.5	ns
t_S	Setup Time, HIGH or LOW, Enable to Clock	5.0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW, Enable to Clock	5.0	1.5	1.5	ns
t_W	$\overline{CP}_n$ Pulse Width, HIGH or LOW	5.0	4.0	4.0	ns
t_W	$\overline{CLR}_n$ Pulse Width, HIGH or LOW	5.0	4.0	4.0	ns
t_{rec}	Recovery Time, $\overline{CLR}_n$ to CP_n	5.0	6.0	6.0	ns

Note 6: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

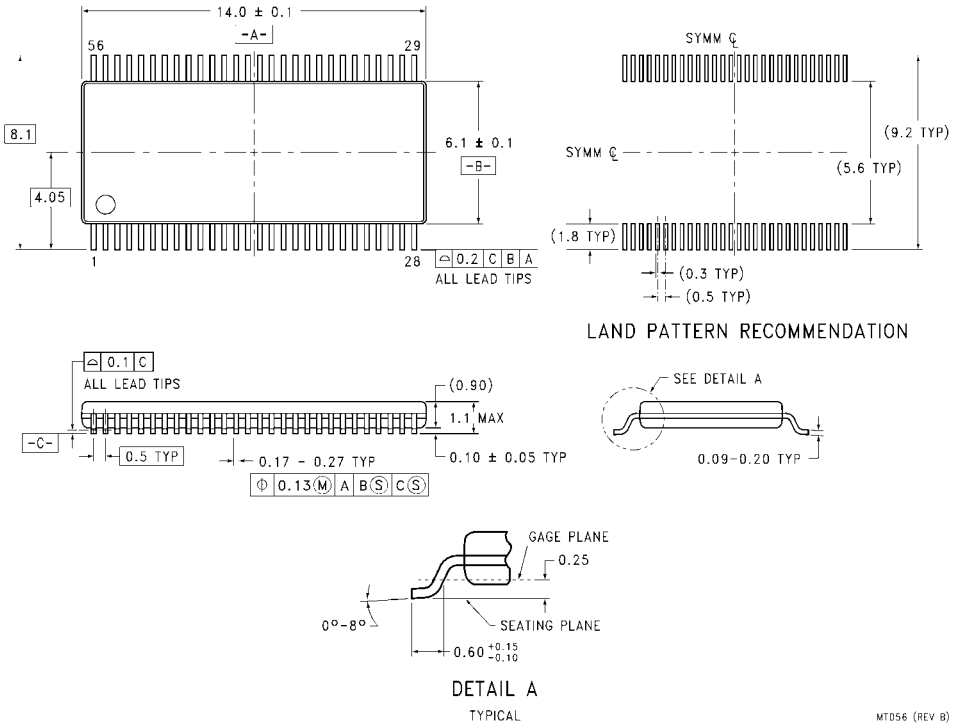
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	95	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT18825
18-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACT18825 contains eighteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 18-bit operation.

Features

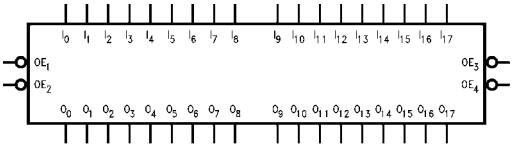
- Broadside pinout allows for easy board layout
- Separate control logic for each byte
- Extra data width for wider address/data paths or buses carrying parity
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

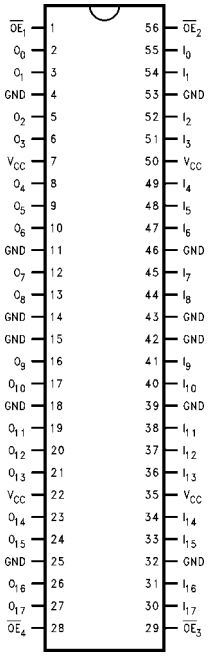
Order Number	Package Number	Package Description
74ACT18825SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT18825MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{17}	Inputs
O_0–O_{17}	Outputs

Functional Description

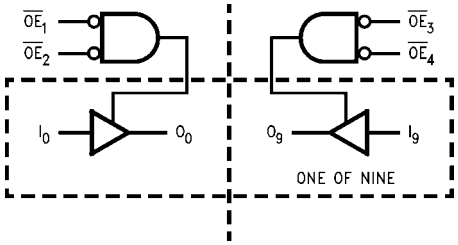
The ACT18825 contains eighteen non-inverting buffers with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independently of the other. The control pins may be shorted together to obtain full 8-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Truth Table

Inputs						Outputs	
Byte 1 (0:8)		Byte 2 (8:17)		I_0–I_8	I_9–I_{17}	O_0–O_8	O_9–O_{17}
$\overline{OE}_1$	$\overline{OE}_2$	$\overline{OE}_3$	$\overline{OE}_4$				
L	L	L	L	H	H	H	H
H	X	L	L	X	L	Z	L
X	H	L	L	X	H	Z	H
L	L	H	X	L	X	L	Z
L	L	X	H	H	X	H	Z
H	H	H	H	X	X	Z	Z
L	L	L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
Per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔVΔt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

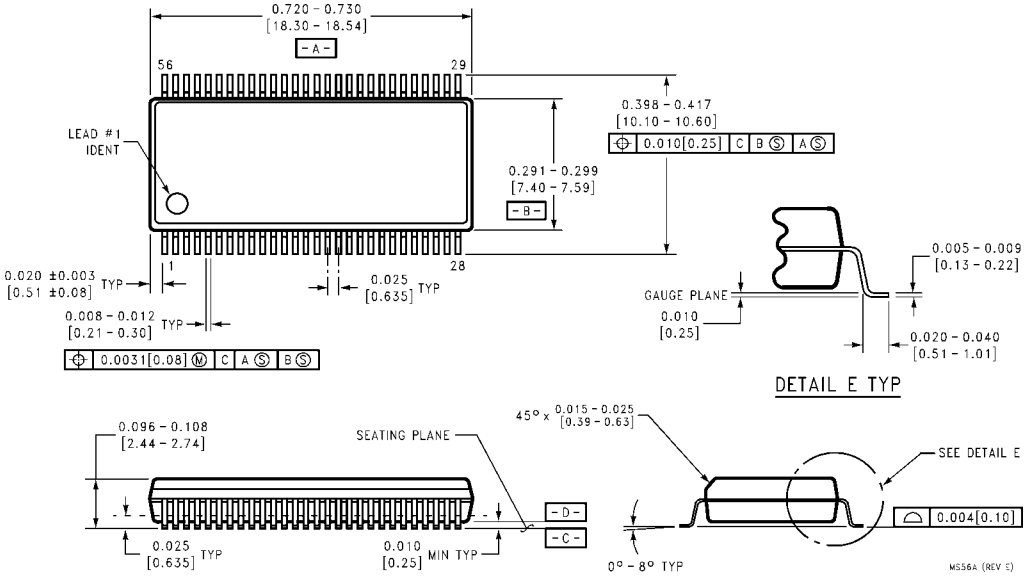
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	2.0	5.3	8.4	2.0	9.0	ns
t_{PLH}	Data to Output		2.0	5.6	8.7	2.0	9.2	
t_{PZL}	Output Enable	5.0	2.0	6.3	9.6	2.0	10.3	ns
t_{PZH}	Time		2.0	6.5	9.7	2.0	10.4	
t_{PLZ}	Output Disable	5.0	1.5	4.5	7.3	1.5	7.6	ns
t_{PHZ}	Time		1.5	5.1	8.5	1.5	8.8	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

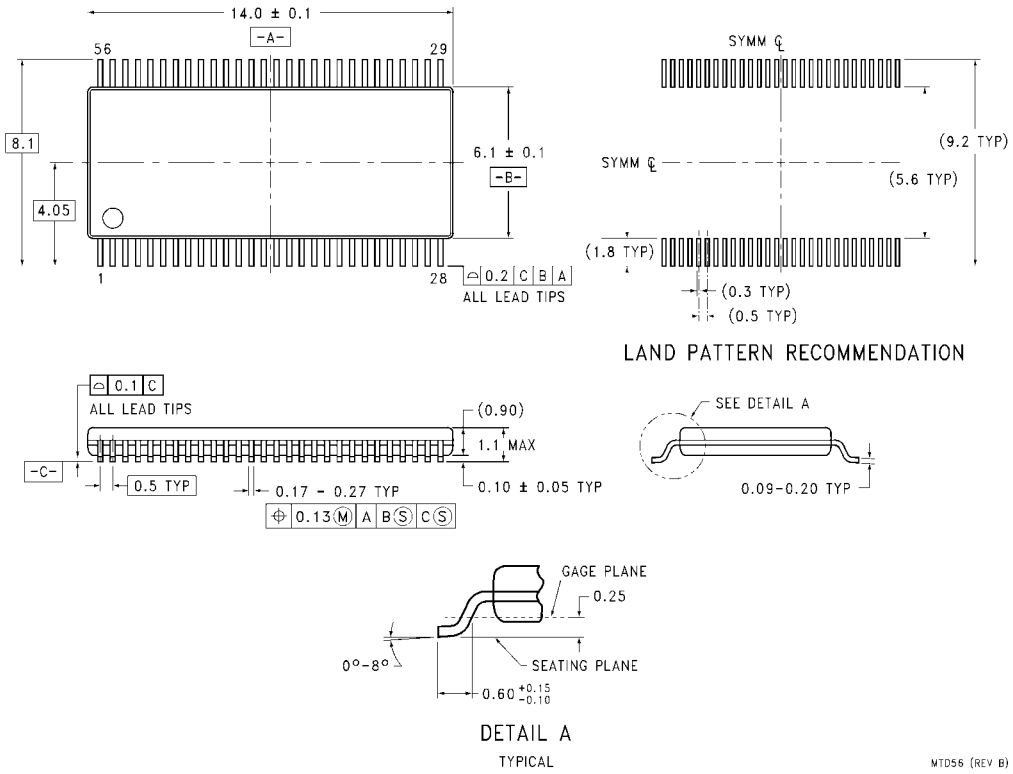
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	95	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74ACT258
Quad 2-Input Multiplexer with 3-STATE Outputs

General Description

The ACT258 is a quad 2-input multiplexer with 3-STATE outputs. Four bits of data from two sources can be selected using a common data select input. The four outputs present the selected data in the complement (inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ($\overline{OE}$) input, allowing the outputs to interface directly with bus-oriented systems.

Features

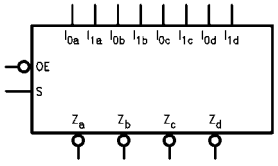
- I_{CC} and I_{OZ} reduced by 50%
- Multiplexer expansion by tying outputs together
- Inverting 3-STATE outputs
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

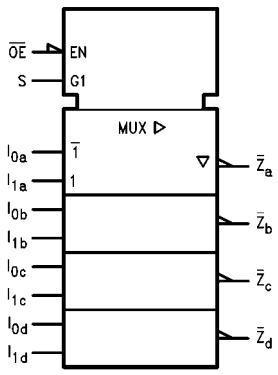
Order Number	Package Number	Package Description
74ACT258SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACT258SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE 11, 5.3mm Wide
74ACT258MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT258PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

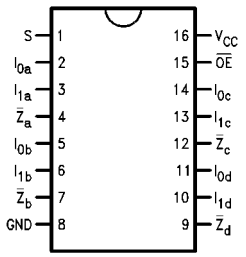
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
S	Common Data Select Input
$\overline{OE}$	3-STATE Output Enable Input
I_{0a}–I_{0d}	Data Inputs from Source 0
I_{1a}–I_{1d}	Data Inputs from Source 1
$\overline{Z}_a$–$\overline{Z}_d$	3-STATE Inverting Data Outputs

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Truth Table

Output Enable	Select Input	Data Inputs		Outputs
$\overline{OE}$	S	I_0	I_1	$\overline{Z}$
H	X	X	X	Z
L	H	X	L	H
L	H	X	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

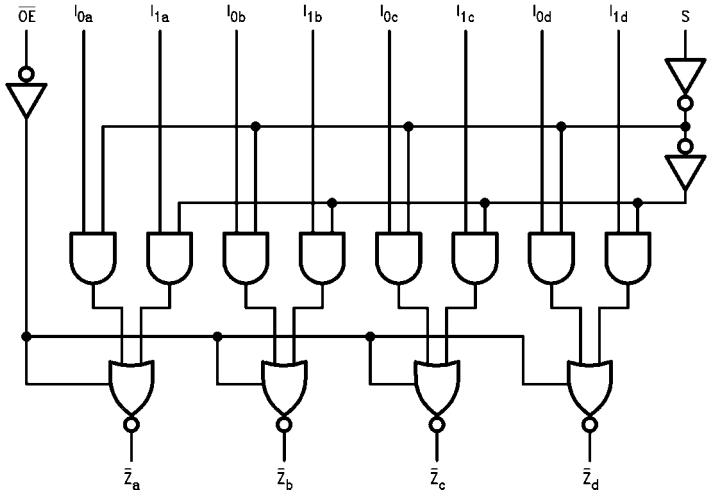
Functional Description

The ACT258 is a quad 2-input multiplexer with 3-STATE outputs. It selects four bits of data from two sources under control of a common Select input (S). When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The data on the selected inputs appears at the outputs in inverted form. The ACT258 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$$\overline{Z}_a = \overline{OE} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$$
$$\overline{Z}_b = \overline{OE} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$$
$$\overline{Z}_c = \overline{OE} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$$
$$\overline{Z}_d = \overline{OE} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$$

When the Output Enable input ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance state. If the outputs of the 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-STATE devices whose outputs are tied together are designed so there is no overlap.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = –0.5V	–20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	–0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = –0.5V	–20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	–0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	–65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	–40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = –40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} – 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} – 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = –50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = –24 mA
		5.5		4.86	4.76		I_{OH} = –24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} – 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			–75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

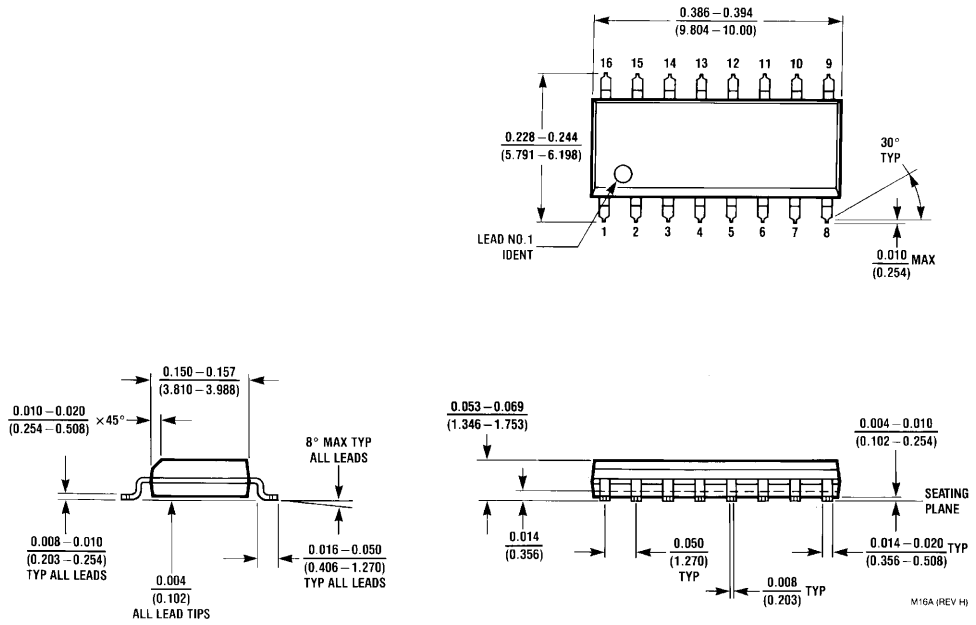
Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay I_n to $\overline{Z}_n$	5.0	2.0	6.5	8.5	1.5	9.5	ns
t_{PHL}	Propagation Delay I_n to $\overline{Z}_n$	5.0	2.0	5.5	7.5	1.5	8.0	ns
t_{PLH}	Propagation Delay S to $\overline{Z}_n$	5.0	3.0	7.5	10.5	2.0	11.5	ns
t_{PHL}	Propagation Delay S to $\overline{Z}_n$	5.0	1.5	7.0	9.5	1.5	11.0	ns
t_{PZH}	Output Enable Time	5.0	2.0	6.5	8.5	1.5	9.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	6.5	8.5	1.5	9.5	ns
t_{PHZ}	Output Disable Time	5.0	1.5	7.0	9.0	1.0	10.0	ns
t_{PLZ}	Output Disable Time	5.0	2.0	6.0	8.0	1.5	9.0	ns

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

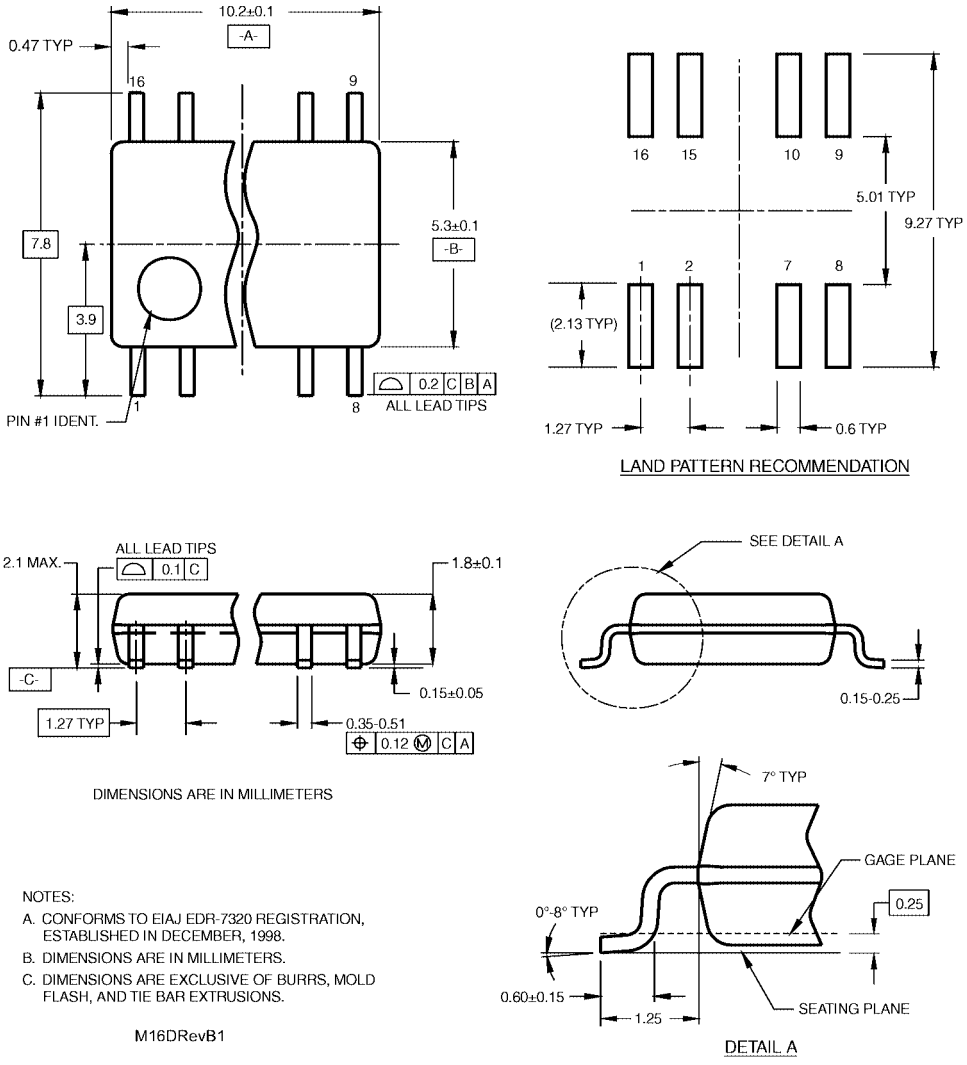
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	55.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

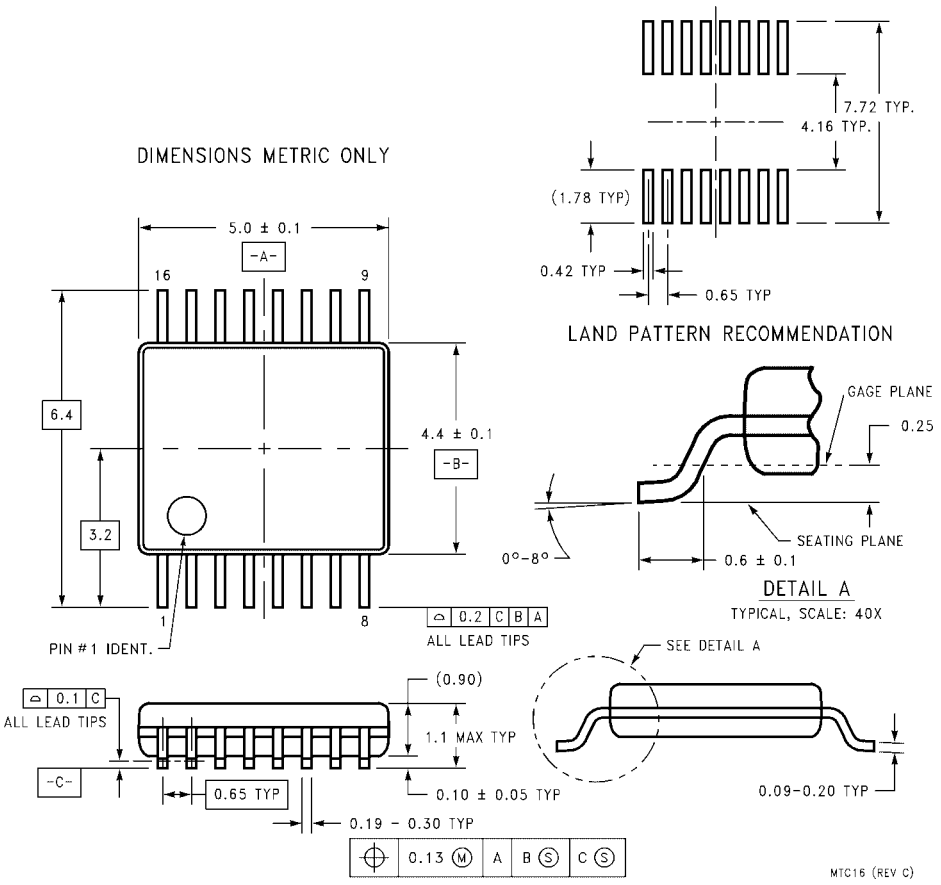
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

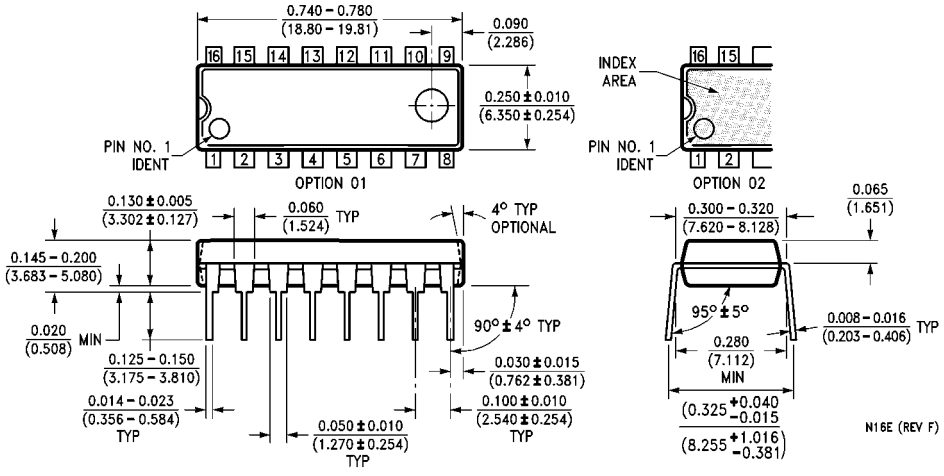
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

February 1989
Revised January 1999

74ACT2708
64 x 9 First-In, First-Out Memory

General Description

The ACT2708 is an expandable first-in, first-out memory organized as 64 words by 9 bits. An 85 MHz shift-in and 60 MHz shift-out typical data rate makes it ideal for high-speed applications. It uses a dual port RAM architecture with pointer logic to achieve the high speed with negligible fall-through time.

Separate Shift-In (SI) and Shift-Out (SO) clocks control the use of synchronous or asynchronous write or read. Other controls include a Master Reset ($\overline{MR}$) and Output Enable ($\overline{OE}$) for initializing the internal registers and allowing the data outputs to be 3-STATE. Input Ready (IR) and Output Ready (OR) signal when the FIFO is ready for I/O operations. The status flags HF and FULL indicate when the FIFO is full, empty or half full.

The FIFO can be expanded to provide different word lengths by tying off unused data inputs.

Features

- 64-words by 9-bit dual port RAM organization
- 85 MHz shift-in, 60 MHz shift-out data rate, typical
- Expandable in word width only
- TTL-compatible inputs
- Asynchronous or synchronous operation
- Asynchronous master reset
- Outputs source/sink 8 mA
- 3-STATE outputs
- Full ESD protection
- Input and output pins directly in line for easy board layout
- TRW 1030 work-alike operation

Applications

- High-speed disk or tape controllers
- A/D output buffers
- High-speed graphics pixel buffer
- Video time base correction
- Digital filtering

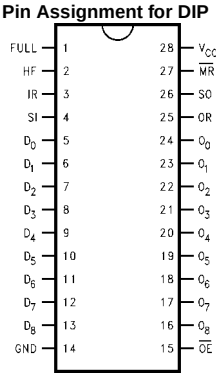
Ordering Code:

Order Number	Package Number	Package Description
74ACT2708PC	N28B	28-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for DIP

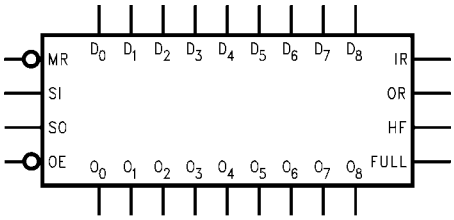


Pin Descriptions

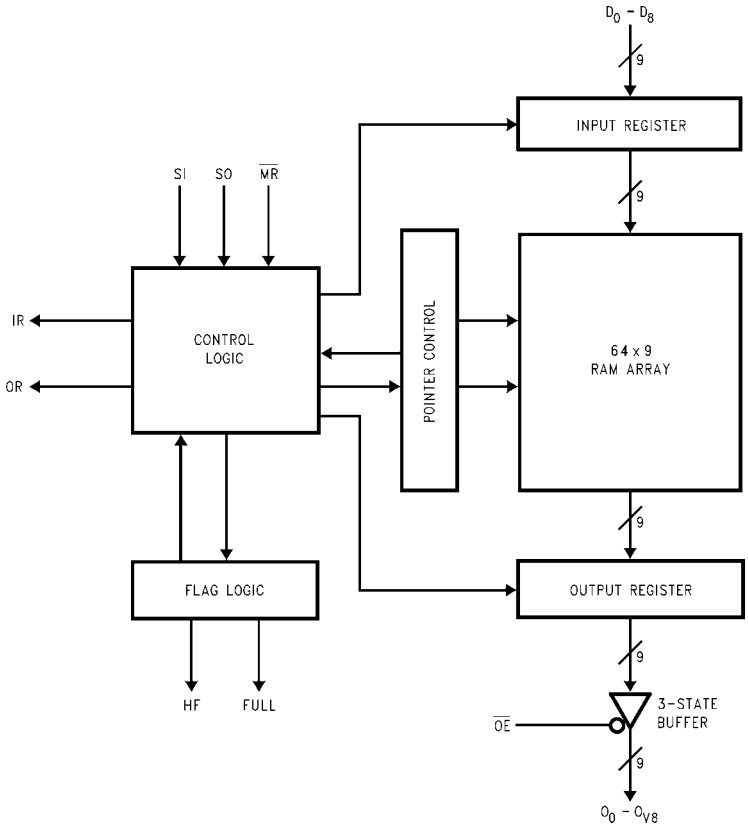
Pin Names	Description
D_0–D_8	Data Inputs
$\overline{MR}$	Master Reset
$\overline{OE}$	Output Enable Input
SI	Shift-In
SO	Shift-Out
IR	Input Ready
OR	Output Ready
HF	Half Full Flag
FULL	Full Flag
O_0–O_8	Data Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Logic Symbol



Block Diagram



Functional Description

INPUTS

Data Inputs (D_0–D_8)

Data inputs for 9-bit wide data are TTL-compatible. Word width can be reduced by trying unused inputs to ground and leaving the corresponding outputs open.

Reset ($\overline{MR}$)

Reset is accomplished by pulsing the $\overline{MR}$ input LOW. During normal operation $\overline{MR}$ is HIGH. A reset is required after power up to guarantee correct operation. On reset, the data outputs go LOW, IR goes HIGH, OR goes LOW, FH and FULL go LOW. During reset, both internal read and write pointers are set to the first location in the array.

Shift-In (SI)

Data is written into the FIFO by pulsing SI HIGH. When Shift-In goes HIGH, the data is loaded into an internal data latch. Data setup and hold times need to be adhered to with respect to the falling edge of SI. The write cycle is complete after the falling edge of SI. The shift-in is independent of any ongoing shift-out operation. After the first word has been written into the FIFO, the falling edge of SI makes HF go HIGH, indicating a non-empty FIFO. The first data word appears at the output after the falling edge of SI. After half the memory is filled, the next rising edge of SI makes FULL go HIGH indicating a half-full FIFO. When the FIFO is full, any further shift-ins are disabled.

When the FIFO is empty and $\overline{OE}$ is LOW, the falling edge of the first SI will cause the first data word just shifted-in to appear at the output, even though SO may be LOW.

Shift-Out (SO)

Data is read from the FIFO by the Shift-Out signal provided the FIFO is not empty. SO going HIGH causes OR to go LOW indicating that output stage is busy. On the falling edge of SO, new data reaches the output after propagation delay t_D. If the last data has been shifted-out of the memory, OR continues to remain LOW, and the last word shifted-out remains on the output pins.

Output Enable ($\overline{OE}$)

$\overline{OE}$ LOW enables the 3-STATE output buffers. When $\overline{OE}$ is HIGH, the outputs are in a 3-STATE mode.

OUTPUTS

Data Outputs (O_0–O_8)

Data outputs are enabled when $\overline{OE}$ is LOW and in the 3-STATE condition when $\overline{OE}$ is HIGH.

Input Ready (IR)

IR HIGH indicates data can be shifted-in. When SI goes HIGH, IR goes LOW, indicating input stage is busy. IR stays LOW when the FIFO is full and goes HIGH after the falling edge of the first shift-out.

Output Ready (OR)

OR HIGH indicates data can be shifted-out from the FIFO. When SO goes HIGH, OR goes LOW, indicating output stage is busy. OR is LOW when the FIFO is reset or empty and goes HIGH after the falling edge of the first shift-in.

Half-Full (HF)

This status flag along with the FULL status flag indicates the degree of fullness of the FIFO. On reset, HF is LOW; it rises on the falling edge of the first SI. The rising edge of the SI pulse that fills up the FIFO makes HF go LOW. Going from the empty to the full state with SO LOW, the falling edge of the first SI causes HF to go HIGH, the rising edge of the 33rd SI causes FULL to go HIGH, and the rising edge of the 64th SI causes HF to go LOW.

When the FIFO is full, HF is LOW and the falling edge of the first shift-out causes HF to go HIGH indicating a "non-full" FIFO.

Full Flag (FULL)

This status flag along with the HF status flag indicates the degree of fullness of the FIFO. On reset, FULL is LOW. When half the memory is filled, on the rising edge of the next SI, the FULL flag goes HIGH. It remains set until the difference between the write pointer and the read pointer is less than or equal to one-half of the total memory of the device. The FULL flag then goes LOW on the rising edge of the next SO.

Status Flags Truth Table

HF	FULL	Status Flag Condition
L	L	Empty
L	H	Full
H	L	<32 Locations Filled
H	H	≥32 Locations Filled

H = HIGH Voltage Level
L = LOW Voltage Level

Reset Truth Table

Inputs			Outputs				
$\overline{MR}$	SI	SO	IR	OR	HF	FULL	O_0–O_8
H	X	X	X	X	X	X	X
L	X	X	H	L	L	L	L

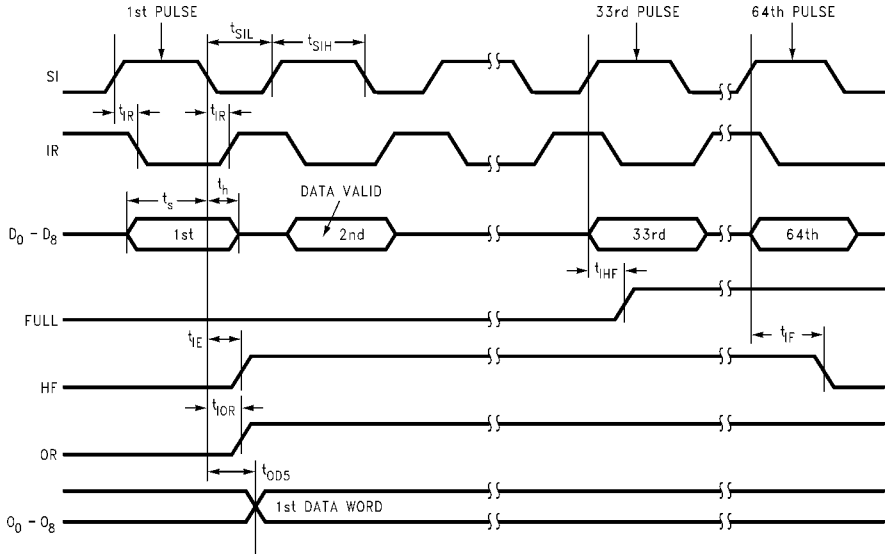
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

MODES OF OPERATION

Mode 1: Shift in Sequence for FIFO Empty to Full

Sequence of Operation

1. Input Ready is initially HIGH; HF and FULL flags are LOW. The FIFO is empty and prepared for valid data. OR is LOW indicating that the FIFO is not yet ready to output data.
2. Shift-In is set HIGH, and data is loaded into the FIFO. Data has to be settled t_s before the falling edge of SI and held t_h after.
3. Input Ready (IR) goes LOW propagation delay t_{IR} after SI goes HIGH: input stage is busy.
4. Shift-In is set LOW; IR goes HIGH indicating the FIFO is ready for additional data. Data just shifted-in arrives at output propagation delay t_{OD5} after SI falls. OR goes HIGH propagation delay t_{IOR} after SI goes LOW, indicating the FIFO has valid data on its outputs. HF goes HIGH propagation delay t_{IE}after SI falls, indicating the FIFO is no longer empty.
5. The process is repeated through the 64th data word. On the rising edge of the 33rd SI, FULL flag goes HIGH propagation delay t_{IHF} after SI, indicating a half-full FIFO. HF goes LOW propagation delay t_{IF} after the rising edge of the 64th pulse indicating that the FIFO is full. Any further shift-ins are disabled.



Note: SO and $\overline{OE}$ are LOW; $\overline{MR}$ is HIGH.

FIGURE 1. Modes of Operation Mode 1

Mode 2: Master Reset

Sequence of Operation

1. Input and Output Ready, HF and FULL can be in any state before the reset sequence with Master Reset ($\overline{MR}$) HIGH.
2. Master Reset goes LOW and clears the FIFO, setting up all essential internal states. Master Reset must be LOW pulse width t_{MRW} before rising again.
3. Master Reset rises.
4. IR rises (if not HIGH already) to indicate ready to write state recovery time t_{MRIRH} after the falling edge of $\overline{MR}$. Both HF and FULL will go LOW indicating an empty FIFO, occurring recovery times t_{MRE} and t_{MRO} respectively after the falling edge of $\overline{MR}$. OR falls recovery time t_{MRORL} after $\overline{MR}$ falls. Data at outputs goes LOW recovery time t_{MRONL} after $\overline{MR}$ goes LOW.
5. Shift-In can be taken HIGH after a minimum recovery time t_{MRSIH} after $\overline{MR}$ goes HIGH.

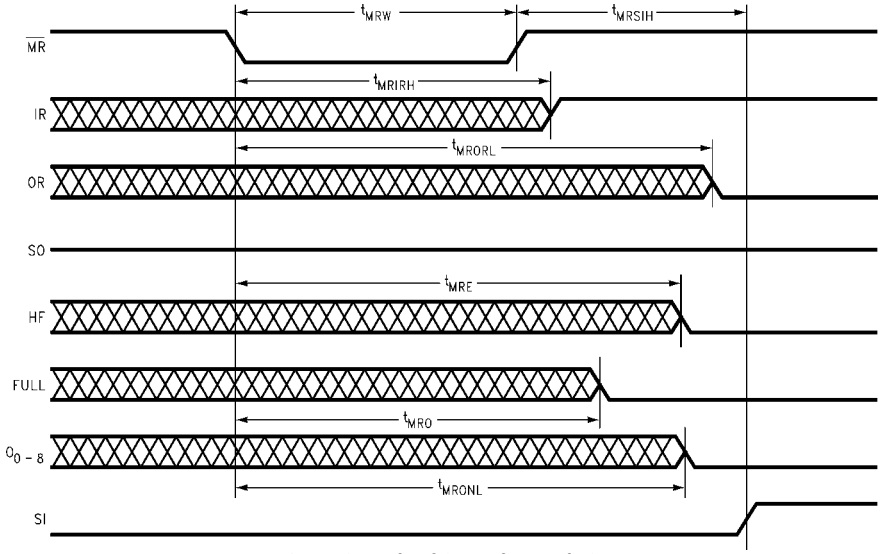
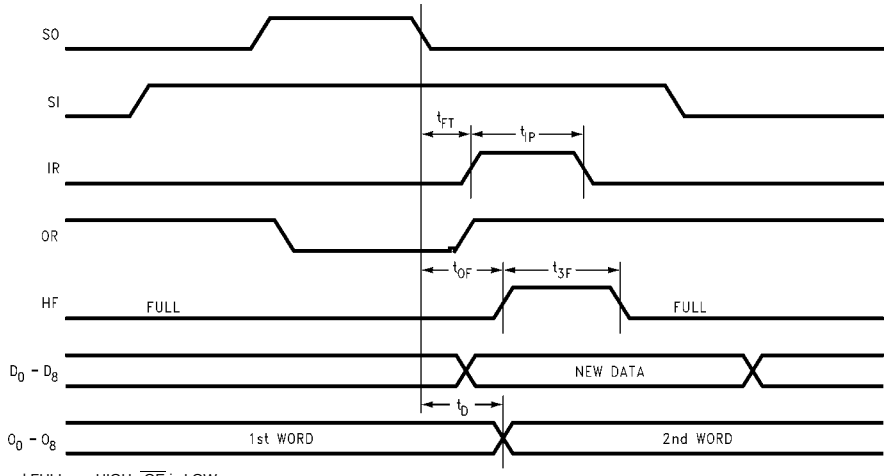


FIGURE 2. Mode of Operation Mode 2

Mode 3: With FIFO Full, Shift-In is Held HIGH in Anticipation of an Empty Location

Sequence of Operation

1. The FIFO is initially full and Shift-In goes HIGH. OR is initially HIGH. Shift-Out is LOW. IR is LOW.
2. Shift-Out is pulsed HIGH, Shift-Out pulse propagates and the first data word is latched on the rising edge of SO. OR falls on this edge. On the falling edge of SO, the second data word appears after propagation delay t_D. New data is written into the FIFO after SO goes LOW.
3. Input Ready goes HIGH one fall-through time, t_{FT}, after the falling edge of SO. Also, HF goes HIGH one t_{OF} after SO falls, indicating that the FIFO is no longer full.
4. IR returns LOW pulse width t_{IP} after rising and shifting new data in. Also, HF returns LOW pulse width t_{3F} after rising, indicating the FIFO is once more full.
5. Shift-In is brought LOW to complete the shift-in process and maintain normal operation.



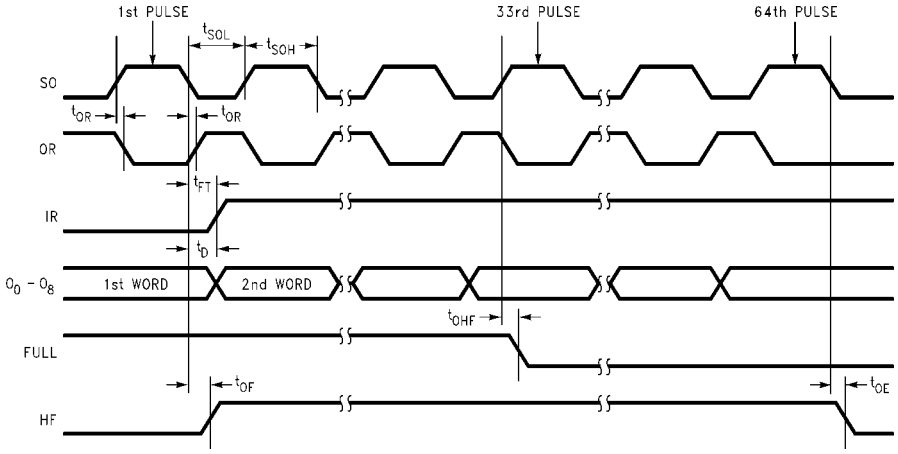
Note: $\overline{MR}$ and FULL are HIGH; $\overline{OE}$ is LOW.

FIGURE 3. Modes of Operation Mode 3

Mode 4: Shift-Out Sequence, FIFO Full to Empty

Sequence of Operation

1. FIFO is initially full and OR is HIGH, indicating valid data is at the output. IR is LOW.
2. SO goes HIGH, resulting in OR going LOW one propagation delay, t_{OR}, after SO rises. OR LOW indicates output stage is busy.
3. SO goes LOW, new data reaches output one propagation delay, t_D, after SO falls; OR goes HIGH one propagation delay, t_{OR}, after SO falls and HF rises one propagation delay, t_{OF}, after SO falls. IR rises one fall-through time, t_{FT}, after SO falls.
4. Repeat process through the 64th SO pulse. FULL flag goes LOW one propagation delay, t_{OHF}, after the rising edge of 33rd SO, indicating that the FIFO is less than half full. On the falling edge of the 64th SO, HF goes LOW one propagation delay, t_{OE}, after SO, indicating the FIFO is empty. The SO pulse may rise and fall again with an attempt to unload an empty FIFO. This results in no change in the data on the outputs as the 64th word stays latched.



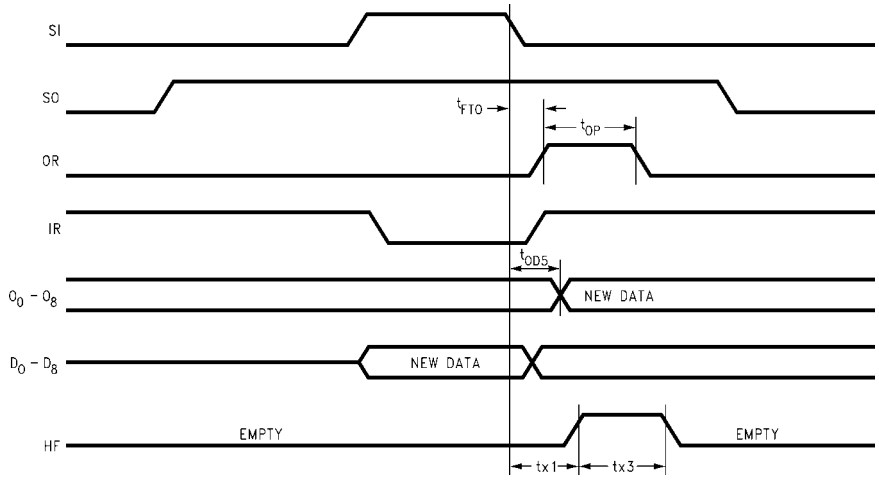
Note: SI and $\overline{OE}$ are LOW; $\overline{MR}$ is HIGH; D_0–D_8 are immaterial.

FIGURE 4. Modes of Operation Mode 4

Mode 5: With FIFO Empty, Shift-Out is Held HIGH in Anticipation of Data

Sequence of Operation

1. FIFO is initially empty; Shift-Out goes HIGH.
2. Shift-In pulse loads data into the FIFO and IR falls. HF rises propagation delay t_{X1} after the falling edge of SI.
3. OR rises a fall-through time of t_{FTO} after the falling edge of Shift-In, indicating that new data is ready to be output.
4. Data arrives at output one propagation delay, t_{OD5}, after the falling edge of Shift-In.
5. OR goes LOW pulse width t_{OP} after rising and HF goes LOW pulse width t_{X3} after rising, indicating that the FIFO is empty once more.
6. Shift-Out goes LOW, necessary to complete the Shift-Out process.



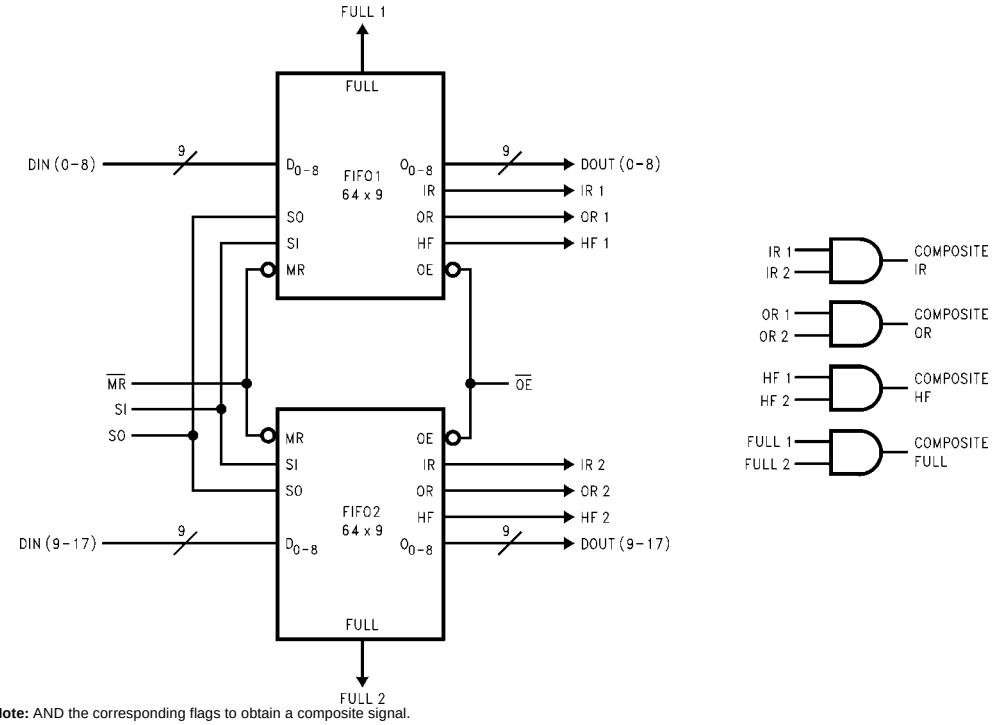
Note: FULL is LOW; $\overline{MR}$is HIGH; $\overline{OE}$ is LOW; $t_{DOF} = t_{FTO} - t_{OD5}$. Data output transition—valid data arrives at output stage t_{DOF} after OR is HIGH.

FIGURE 5. Modes of Operation Mode 5

FIFO Expansion

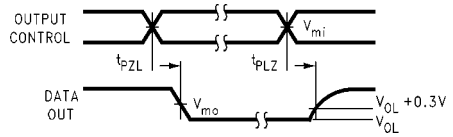
Word Width Expansion

Word width can be increased by connecting the corresponding input control signals of multiple devices. Flags can be monitored to obtain a composite signal by ANDing the corresponding flags.



Note: AND the corresponding flags to obtain a composite signal.

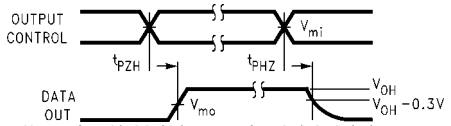
FIGURE 6. Word Width Expansion—64 x 18 FIFO



V_{mi} = 50% V_{DD} for AC/ACQ devices; 1.5V for ACT/ACTQ devices

V_{mo} = 50% V_{DD} for AC/ACT, ACQ/ACTQ devices

FIGURE 7. 3-STATE Output Low Enable and Disable Times for AC/ACT, ACQ/ACTQ



V_{mi} = 50% V_{DD} for AC/ACQ devices; 1.5V for ACT/ACTQ devices

V_{mo} = 50% V_{DD} for AC/ACT, ACQ/ACTQ devices

FIGURE 8. 3-STATE Output High Enable and Disable Times for AC/ACT, ACQ/ACTQ

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±32 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±32 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C Typ	T_A = −40° to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8		V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum High Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −8 mA
		5.5		4.86	4.76		I_{OH} = −8 mA (Note 2)
V_{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 8 mA
		5.5		0.36	0.44		I_{OL} = 8 mA (Note 2)
I_{IN}	Maximum Input	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	µA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6	1.0	1.5	mA	V_I = V_{CC} −2.1V
I_{OLD}	Maximum Dynamic Output Current (Note 3)	5.5			32	mA	V_{OLD} = 1.65V
I_{OHD}		5.5			−32	mA	V_{OHD} = 3.85V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80	µA	V_{IN} = V_{CC} or GND
I_{CCD}	Supply Current 20 MHz Loaded	5.5	125	150	150	mA	f = 20 MHz (Note 4)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Test load 50 pF, 500Ω to ground

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay, t_{IR} SI to IR	5.0	2.0	6.5	11.0	1.5	12.5	ns
t_{PHL}	Propagation Delay, t_{IR} SI to IR	5.0	2.0	6.5	11.0	1.5	12.0	ns
t_{PLH}	Propagation Delay, t_{IHF} SI to > HF	5.0	4.0	10.5	17.0	4.0	19.5	ns
t_{PHL}	Propagation Delay, t_{IF} SI to Full Condition	5.0	4.5	10.5	16.5	4.5	19.5	ns
t_{PLH}	Propagation Delay, t_{IE} SI to Not Empty	5.0	4.0	10.0	15.5	4.0	17.5	ns
t_{PLH}	Propagation Delay, t_{IOR} SI to OR	5.0	4.0	13.5	16.5	4.0	19.0	ns
t_{PLH}	Propagation Delay t_{MRIRH} $\overline{MR}$ to IR	5.0	3.0	8.5	13.5	3.0	15.5	ns
t_{PHL}	Propagation Delay, t_{MRORL} $\overline{MR}$ to OR	5.0	7.0	16.5	25.5	7.0	29.0	ns
t_{PHL}	Propagation Delay, t_{MRO} $\overline{MR}$ to Full Flag	5.0	3.5	9.0	14.0	3.5	16.0	ns
t_{PHL}	Propagation Delay, t_{MRE} $\overline{MR}$ to HF Flag	5.0	8.0	17.5	27.5	8.0	30.5	ns
t_{PHL}	Propagation Delay, t_{MRONL} $\overline{MR}$ to O_n, LOW	5.0	3.0	9.0	15.0	3.0	17.0	ns
t_{PLH}	Propagation Delay, t_D SO to Data Out	5.0	6.5	18.5	27.0	6.5	31.0	ns
t_{PHL}	Propagation Delay, t_D SO to Data Out	5.0	6.5	18.5	29.5	6.5	34.5	ns
t_{PHL}	Propagation Delay, t_{OHF} SO to < HF	5.0	3.5	8.5	13.5	3.5	15.5	ns
t_{PLH}	Propagation Delay, t_{OF} SO to Not Full	5.0	5.0	12.5	19.5	5.0	22.0	ns
t_{PLH}, t_{PHL}	Propagation Delay, t_{OR} SO to OR	5.0	2.5	7.0	11.5	2.5	13.5	ns
t_{PHL}	Propagation Delay, t_{OE} SO to Empty	5.0	3.5	9.5	15.5	3.0	17.5	ns
t_{PLH}	Propagation Delay, t_{OD5} SI to New Data Out	5.0	7.0	19.0	30.5	6.0	35.5	ns
t_{PHL}	Propagation Delay, t_{OD5} SI to New Data Out	5.0	7.0	19.0	29.5	6.0	34.5	ns
t_{PLH}	Propagation Delay, t_{X1} SI to HF	5.0	3.5	10.0	16.0	2.5	18.0	ns
t_{PLH}	Fall-Through Time, t_{FTO} SI to OR	5.0	3.5	13.5	21.0	1.5	24.0	ns
t_W	R Pulse Width, t_{OP}	5.0	12.5	17.0	26.0	12.5	30.5	ns

AC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_W	HF Pulse Width, t_{X3}	5.0	14.5	20.5	30.5	14.5	36.5	ns
t_W	IR Pulse Width, t_{IP}	5.0	16.5	28.0	43.0	16.5	51.5	ns
t_W	HF Pulse Width, t_{3F}	5.0	17.5	30.0	46.5	17.5	56.0	ns
t_{PLH}	Fall-Through Times, t_{FT} SO to IR	5.0	6.0	15.0	23.5	2.5	28.0	ns
t_{PZL}	Output Enable $\overline{OE}$ to O_n	5.0	2.0	6.5	11.0	1.5	12.0	ns
t_{PLZ}	Output Disable $\overline{OE}$ to O_n	5.0	1.5	5.0	8.5	1.5	9.5	ns
t_{PZH}	Output Enable $\overline{OE}$ to O_n	5.0	2.0	7.0	12.0	1.5	13.0	ns
t_{PHZ}	Output Disable $\overline{OE}$ to O_n	5.0	1.5	7.0	12.0	1.5	13.0	ns
f_{SI}	Maximum SI Clock Frequency	5.0	55	85		45		MHz
f_{SO}	Maximum SO Clock Frequency	5.0	42	60		35		MHz

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements

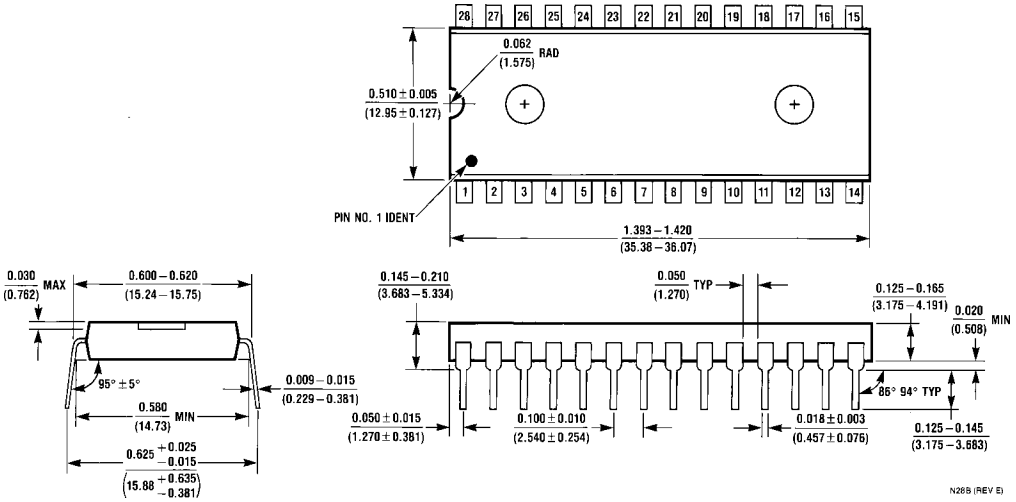
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
$t_W(H)$	SI Pulse Width, t_{SIH}	5.0	3.5	6.5	7.5	ns
$t_W(L)$	SI Pulse Width, t_{SIL}	5.0	6.0	10.0	12.0	ns
t_S	Setup Time, HIGH or LOW, D_n to SI	5.0	1.0	3.5	4.5	ns
t_H	Hold Time, HIGH or LOW, D_n to SI	5.0	1.5	3.5	4.5	ns
t_W	$\overline{MR}$ Pulse Width, t_{MRW}	5.0	13.0	20.0	24.5	ns
t_{rec}	Recovery Time, t_{MRSIH} $\overline{MR}$ to SI	5.0	4.5	7.5	8.5	ns
$t_W(H)$	SO Pulse Width, t_{SOH}	5.0	7.5	6.5	8.0	ns
$t_W(L)$	SO Pulse Width, t_{SOL}	5.0	9.0	14.0	17.0	ns

Note 6: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	20.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



28-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600" Wide
Package Number N28B

FAIRCHILD SEMICONDUCTOR™

June 1988
Revised October 1998

74ACT323
8-Bit Universal Shift/Storage Register with Synchronous Reset and Common I/O Pins

General Description

The ACT323 is an 8-bit universal shift/storage register with 3-STATE outputs. Parallel load inputs and flip-flop outputs are multiplexed to minimize pin count. Separate serial inputs and outputs are provided for Q_0 and Q_7 to allow easy cascading. Four operation modes are possible: hold (store), shift left, shift right and parallel load.

Features

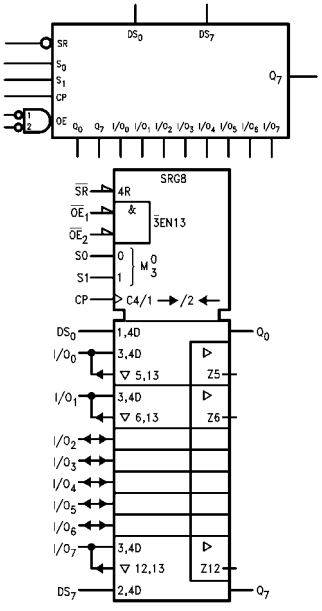
- I_{CC} and I_{OZ} reduced by 50%
- Common parallel I/O for reduced pin count
- Additional serial inputs and outputs for expansion
- Four operating modes: shift left, shift right, load and store
- 3-STATE outputs for bus-oriented applications
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74ACT323PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

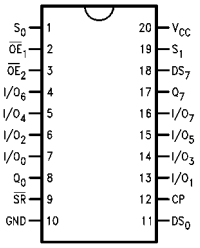
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram

Pin Assignment for DIP



Pin Descriptions

Pin Name	Description
CP	Clock Pulse Input
DS_0	Serial Data Input for Right Shift
DS_7	Serial Data Input for Left Shift
S_0, S_1	Mode Select Inputs
$\overline{SR}$	Synchronous Reset Input
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I/O_0–I/O_7	Multiplexed Parallel Data Inputs or 3-STATE Parallel Data Outputs
Q_0, Q_7	Serial Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT323 contains eight edge-triggered D-type flip-flops and the interstage logic necessary to perform synchronous reset, shift left, shift right, parallel load and hold operations. The type of operation is determined by S_0 and S_1 as shown in the Mode Select Table. All flip-flop outputs are brought out through 3-STATE buffers to separate I/O pins that also serve as data inputs in the parallel load mode. Q_0 and Q_7 are also brought out on other pins for expansion in serial shifting of longer words.

A LOW signal on $\overline{SR}$ overrides the Select inputs and allows the flip-flops to be reset by the next rising edge of CP. All other state changes are also initiated by the LOW-to-HIGH CP transition. Inputs can change when the clock is in either state provided only that the recommended setup and hold times, relative to the rising edge of CP, are observed.

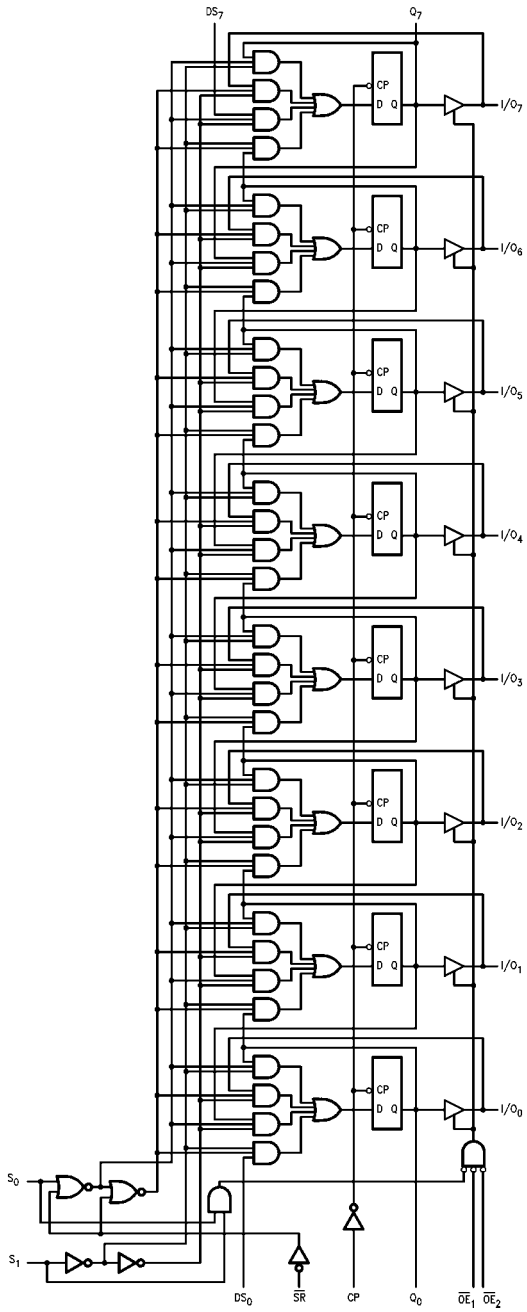
A HIGH signal on either $\overline{OE}_1$ or $\overline{OE}_2$ disables the 3-STATE buffers and puts the I/O pins in the high impedance state. In this condition the shift, load, hold and reset operations can still occur. The 3-STATE buffers are also disabled by HIGH signals on both S_0 and S_1 in preparation for a parallel load operation.

Mode Select Table

Inputs				Response
$\overline{SR}$	S_1	S_0	CP	
L	X	X	⌐	Synchronous Reset; Q_0–Q_7 = LOW
H	H	H	⌐	Parallel Load; $I/O_n \rightarrow Q_n$
H	L	H	⌐	Shift Right; $DS_0 \rightarrow Q_0$, $Q_0 \rightarrow Q_1$, etc.
H	H	L	⌐	Shift Left; $DS_7 \rightarrow Q_7$, $Q_7 \rightarrow Q_6$, etc.
H	L	L	X	Hold

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or	
Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum High Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum Low Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum High Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum Low Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = −24 mA
		5.5		0.36	0.44		I_{OL} = −24 mA (Note 2)
I_{IN}	Maximum Input	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
	Leakage Current						
I_{OZT}	Maximum I/O	5.5		±0.3	±3.0	μA	$V_{I/O}$ = V_{CC} or GND
	Leakage Current						V_{IN} = V_{IH}, V_{IL}
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
	Supply Current						

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = 25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Input Frequency	5.0	120	125		110		MHz
t_{PLH}	Propagation Delay CP to Q_0 or Q_7	5.0	5.0	9.0	12.5	4.0	14.0	ns
t_{PHL}	Propagation Delay CP to Q_0 or Q_7	5.0	5.0	9.0	13.5	4.5	15.0	ns
t_{PLH}	Propagation Delay CP to I/O_n	5.0	5.0	8.5	12.5	4.5	14.5	ns
t_{PHL}	Propagation Delay CP to I/O_n	5.0	6.0	10.0	14.5	5.0	16.0	ns
t_{PZH}	Output Enable Time	5.0	3.5	7.5	11.0	3.0	12.5	ns
t_{PZL}	Output Enable Time	5.0	3.5	7.5	11.5	3.0	13.0	ns
t_{PHZ}	Output Disable Time	5.0	4.0	8.5	12.5	3.0	13.5	ns
t_{PLZ}	Output Disable Time	5.0	3.0	8.0	11.5	2.5	12.5	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

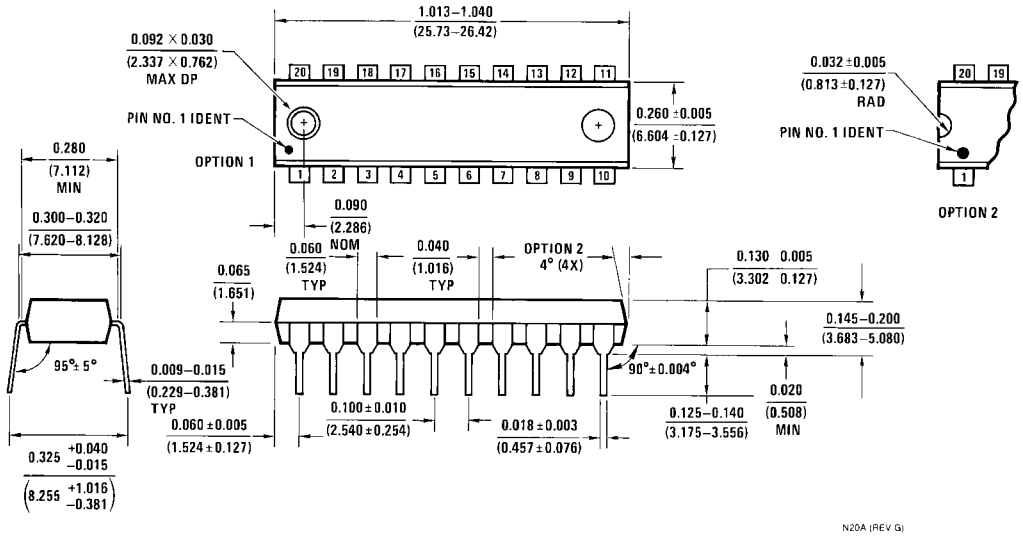
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = 25°C$, $C_L = 50$ pF, $V_{CC} = +5.0V$		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $V_{CC} = +5.0V$	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW S_0 or S_1 to CP	5.0	2.0	5.0	5.0	ns
t_H	Hold Time, HIGH or LOW S_0 or S_1 to CP	5.0	0	1.5	1.5	ns
t_S	Setup Time, HIGH or LOW I/O_n, DS_0, DS_7 to CP	5.0	1.0	4.0	4.5	ns
t_H	Hold Time, HIGH or LOW I/O_n, DS_0, DS_7 to CP	5.0	0	1.0	1.0	ns
t_S	Setup Time, HIGH or LOW $\overline{SR}$ to CP	5.0	1.0	2.5	2.5	ns
t_H	Hold Time, HIGH or LOW $\overline{SR}$ to CP	5.0	0	1.0	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.0	4.0	4.5	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	170	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT533
Octal Transparent Latch with 3-STATE Outputs

General Description

The ACT533 consists of eight latches with 3-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is low, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the bus output is in the high impedance state.

Features

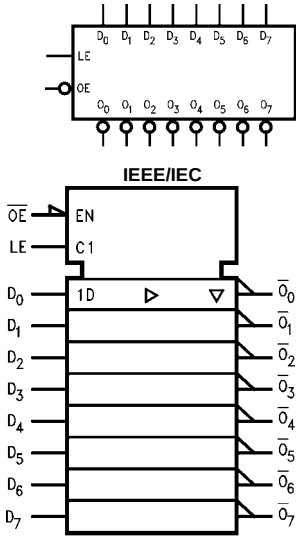
- I_{CC} and I_{OZ} reduced by 50%
- Eight latches in a single package
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Inverted version of the ACT373
- TTL-compatible inputs

Ordering Code:

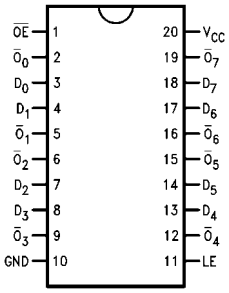
Order Number	Package Number	Package Description
74ACT533SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT533MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT533PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
$\overline{O}_0$–$\overline{O}_7$	3-STATE Latch Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

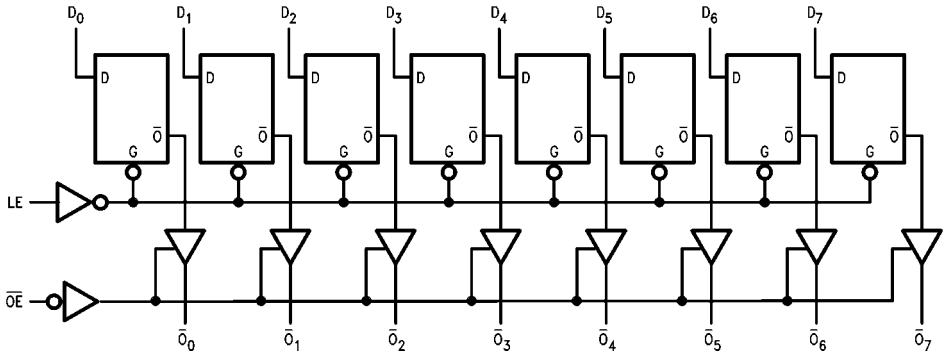
The ACT533 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**$\overline{O}_n$**
X	H	X	Z
H	L	L	H
H	L	H	L
L	L	X	$\overline{O}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
$\overline{O}_0$ = Previous $\overline{O}_0$ before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	− 0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	− 20 mA
V_I = V_{CC} + 0.5V	+ 20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = − 0.5V	− 20 mA
V_O = V_{CC} + 0.5V	+ 20 mA
DC Output Voltage (V_O)	− 0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	− 65°C to + 150°C
DC Latchup Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay D_n to O_n	5.0	2.0	6.0	8.0	2.0	8.5	ns
t_{PHL} t_{PLH}	Propagation Delay LE to O_n	5.0	2.5	7.0	9.0	2.5	9.5	ns
t_{PZL}, t_{PZH}	Output Enable Time	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PHZ}, t_{PLZ}	Output Disable Time	5.0	1.0	8.0	10.0	1.0	10.5	ns

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

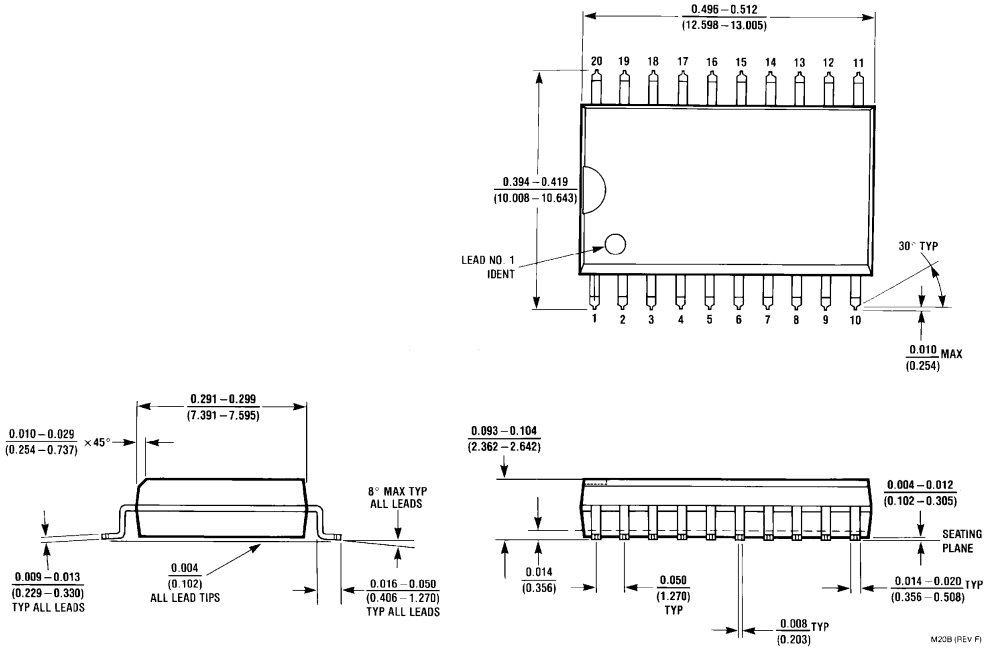
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0	1.5	1.5	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	4.0	4.0	ns

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

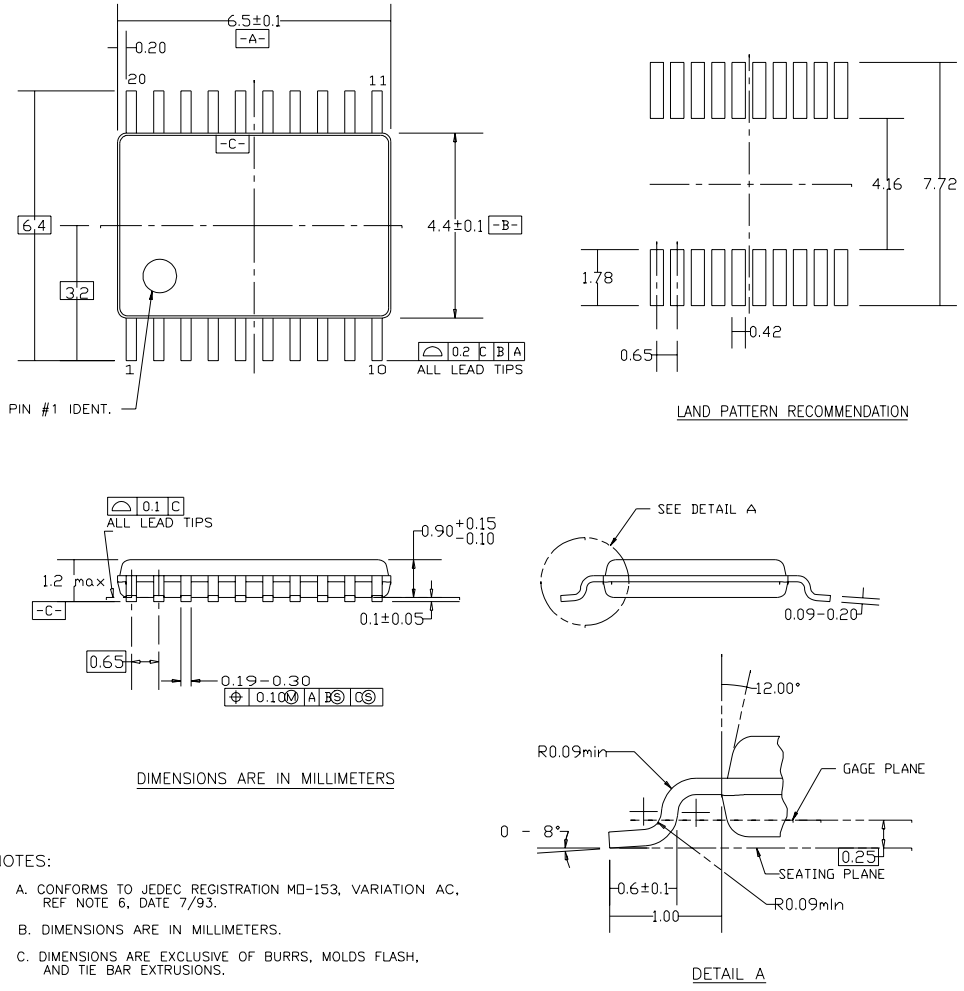
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

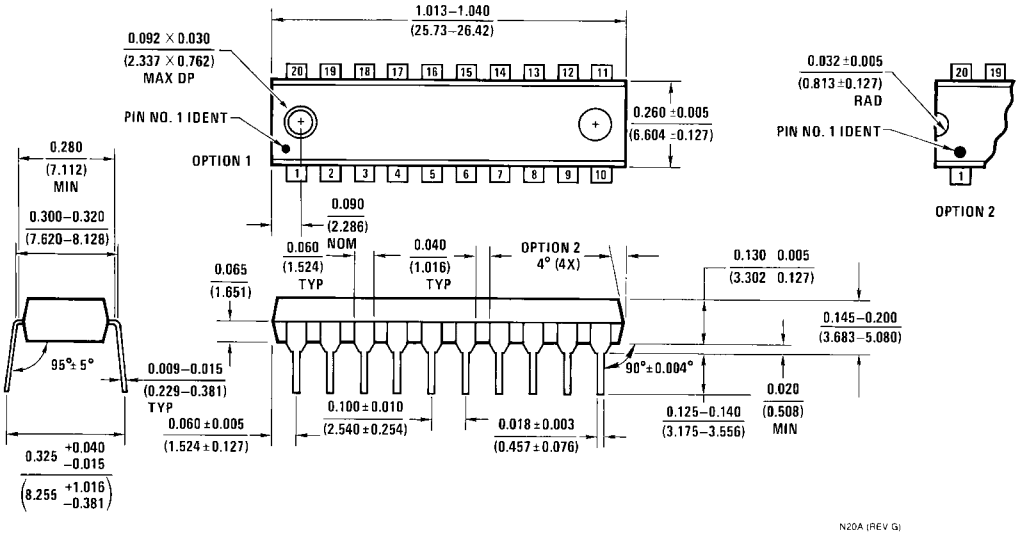
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package, JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1999

74ACT534
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACT534 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops. The ACT534 is the same as the ACT374 except that the outputs are inverted.

Features

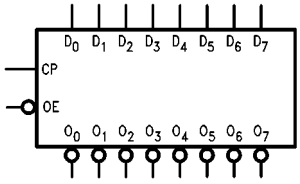
- I_{CC} and I_{OZ} reduced by 50%
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- 3-STATE outputs for bus-oriented applications
- Outputs source/sink 24 mA
- ACT534 has TTL-compatible inputs
- Inverted output version of ACT374

Ordering Code:

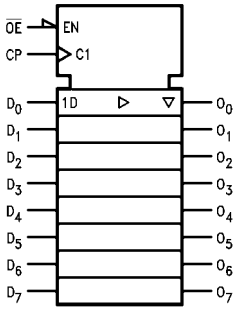
Order Number	Package Number	Package Description
74ACT534SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT534SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACT534PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

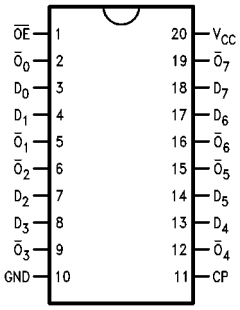
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
$\overline{O}_0$–$\overline{O}_7$	Complementary 3-STATE Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

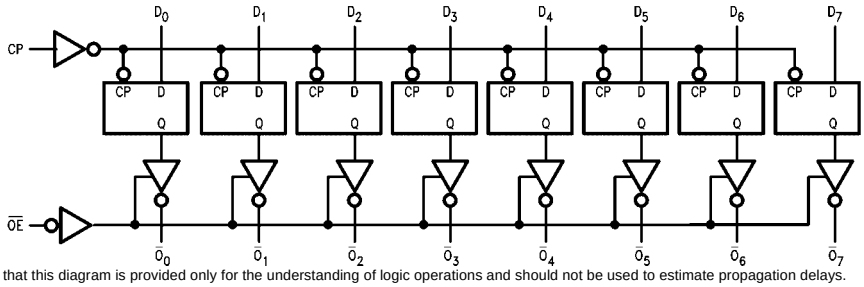
The ACT534 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE complementary outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Output
CP	**OE**	**D**	$\overline{\mathbf{O}}$
⌐‾	L	H	L
⌐‾	L	L	H
L	L	X	$\overline{O}_0$
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐‾ = LOW-to-HIGH Clock Transition
Z = High Impedance
$\overline{O}_0$ = Value stored from previous clock cycle

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0		100		120		MHz
t_{PLH}	Propagation Delay CP to $\overline{Q}_n$	5.0	2.5	6.5	11.5	2.0	12.5	ns
t_{PHL}	Propagation Delay CP to $\overline{Q}_n$	5.0	2.0	6.0	10.5	2.0	12.0	ns
t_{PZH}	Output Enable Time	5.0	2.5	6.5	12.0	2.0	12.5	ns
t_{PZL}	Output Enable Time	5.0	2.0	6.0	11.0	2.0	11.5	ns
t_{PHZ}	Output Disable Time	5.0	1.5	7.0	12.5	1.0	13.5	ns
t_{PLZ}	Output Disable Time	5.0	1.5	5.5	10.5	1.0	10.5	ns

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements

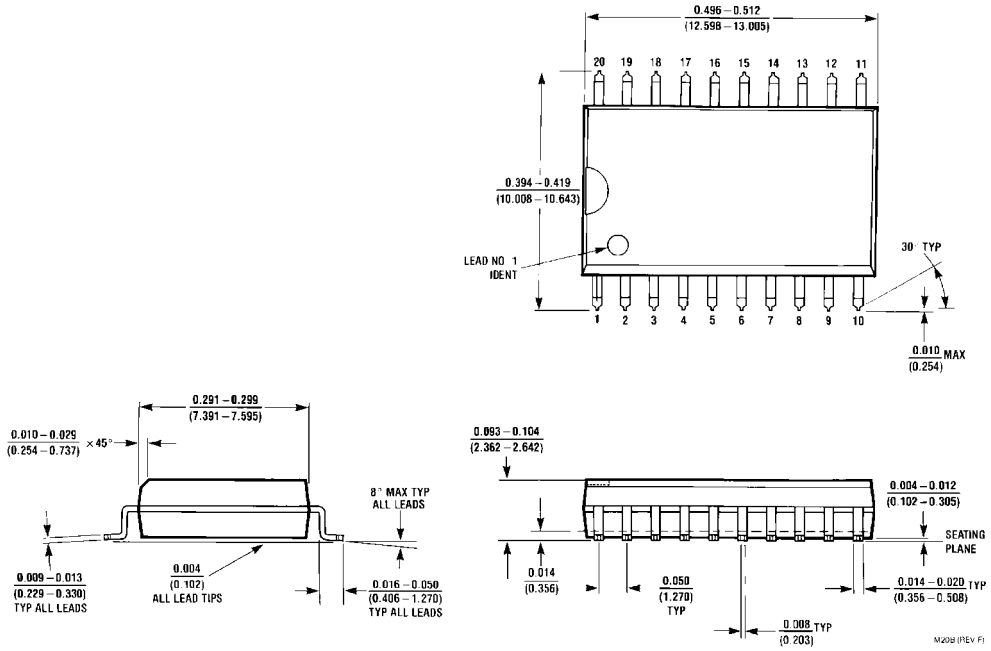
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	1.0	3.5	4.0	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	−1.0	1.0	1.5	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.0	3.5	3.5	ns

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

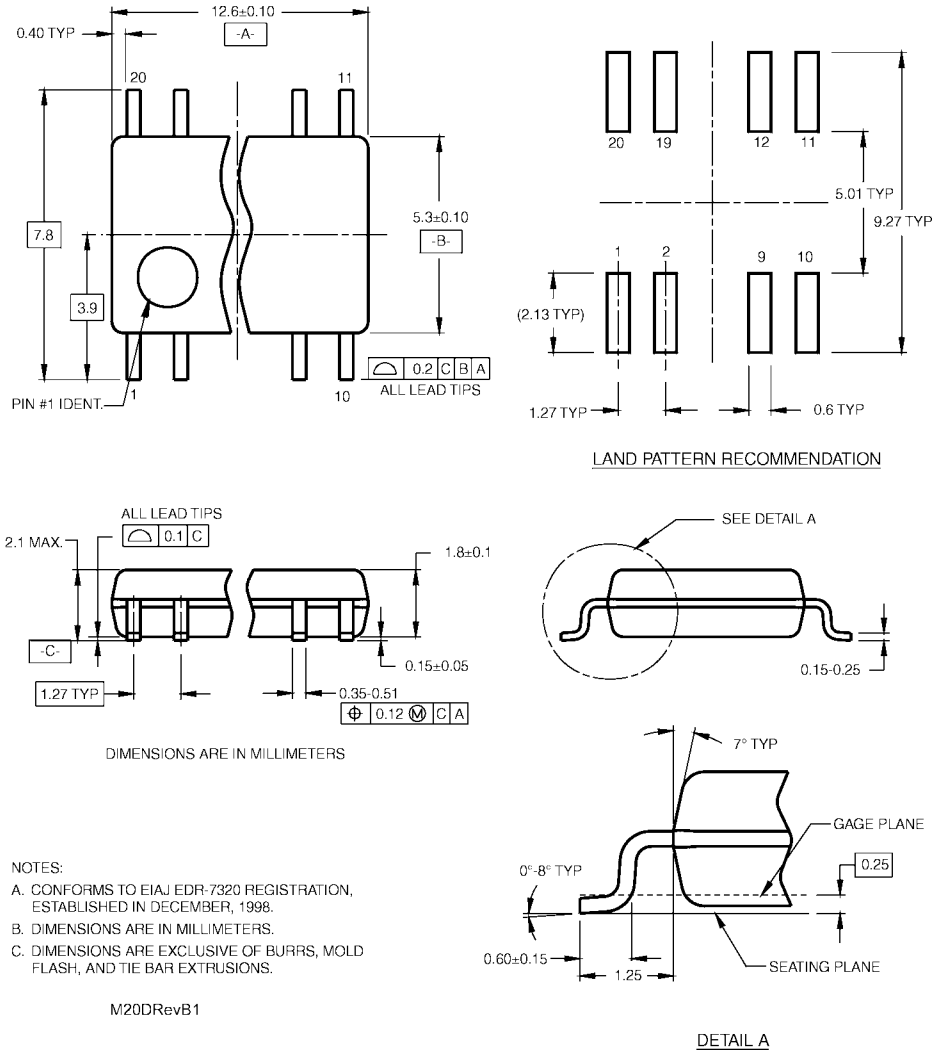
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

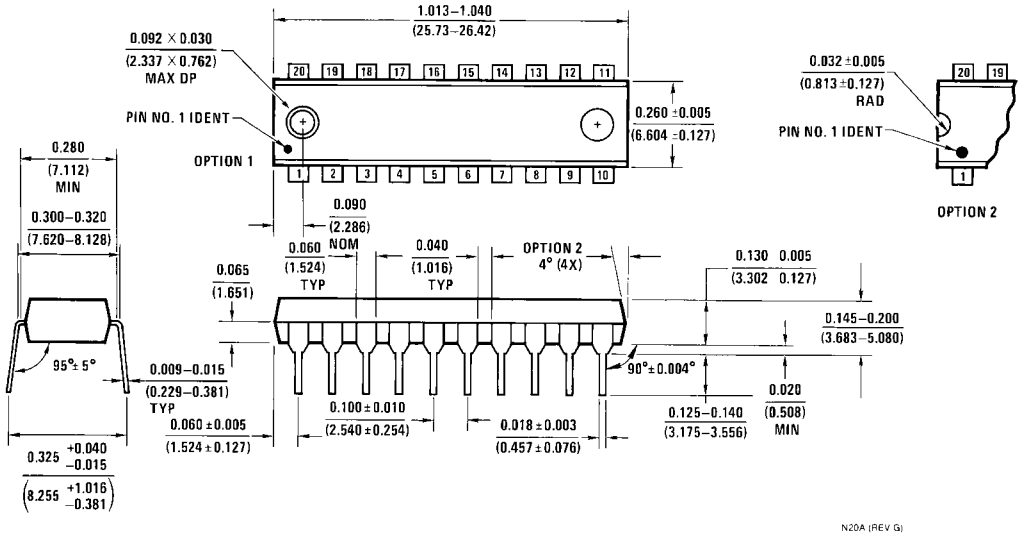
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised December 1998

74ACT563
Octal Latch with 3-STATE Outputs

General Description

The ACT563 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

The ACT563 device is functionally identical to the ACT573, but with inverted outputs.

Features

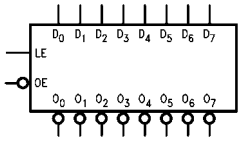
- I_{CC} and I_{OZ} reduced by 50%
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to ACT573 but with inverted outputs
- Outputs source/sink 24 mA
- ACT563 has TTL-compatible inputs

Ordering Code:

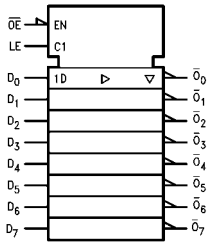
Order Number	Package Number	Package Description
74ACT563SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols

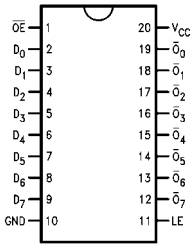


IEEE/IEC



Connection Diagram

Pin Assignment for SOIC



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
$\overline{O}_0$–$\overline{O}_7$	3-STATE Latch Outputs

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

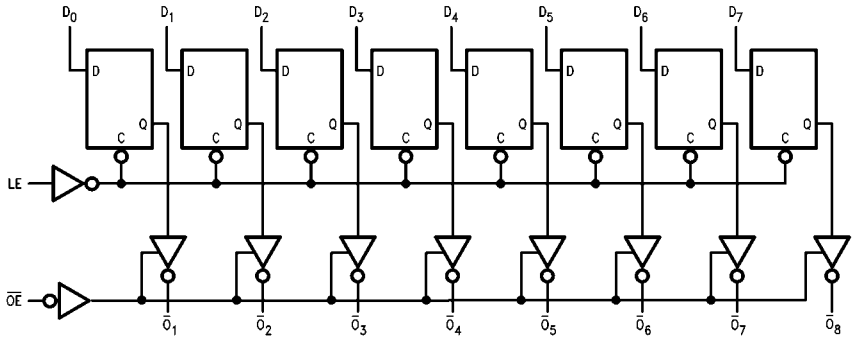
The ACT563 contains eight D-type latches with 3-STATE complementary outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but that does not interfere with entering new data into the latches.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	LE	D	Q	O	
H	X	X	X	Z	High-Z
H	H	L	H	Z	High-Z
H	H	H	L	Z	High-Z
H	L	X	NC	Z	Latched
L	H	L	H	H	Transparent
L	H	H	L	L	Transparent
L	L	X	NC	NC	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
(PDIP)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to $\overline{O}_n$	5.0	3.0	7.0	11.5	2.5	12.5	ns
t_{PHL}	Propagation Delay D_n to $\overline{O}_n$	5.0	3.0	6.0	10.0	2.5	11.0	ns
t_{PLH}	Propagation Delay LE to $\overline{O}_n$	5.0	3.0	6.5	10.5	2.5	11.5	ns
t_{PHL}	Propagation Delay LE to $\overline{O}_n$	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PZH}	Output Enable Time	5.0	2.5	5.5	9.0	2.0	10.0	ns
t_{PZL}	Output Enable Time	5.0	2.0	5.5	8.5	2.0	9.5	ns
t_{PHZ}	Output Disable Time	5.0	3.5	6.5	10.5	2.5	11.5	ns
t_{PLZ}	Output Disable Time	5.0	2.0	4.5	8.0	1.0	8.5	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

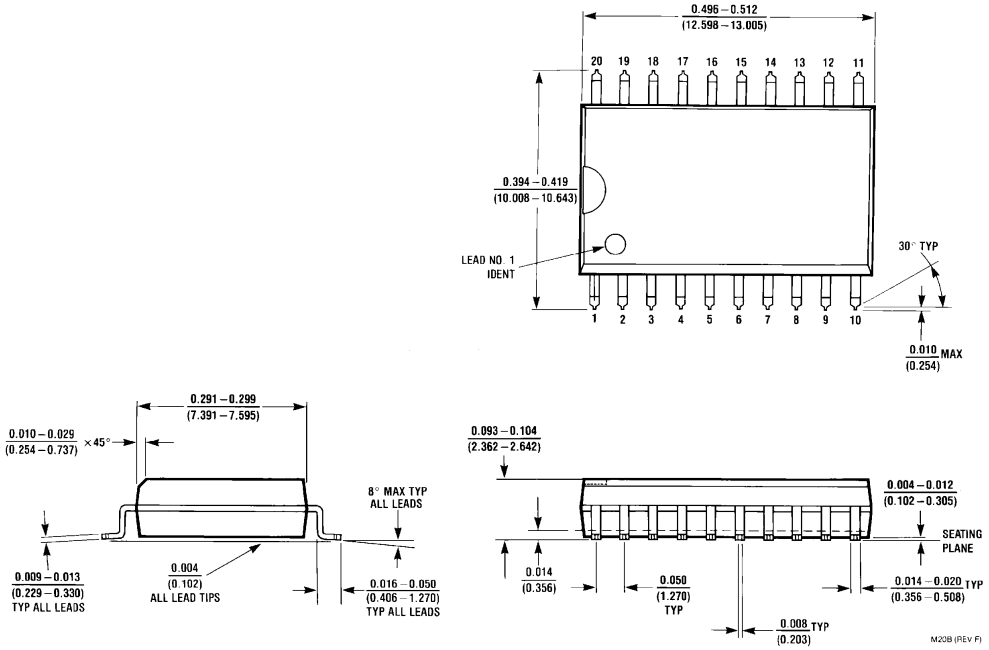
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_s	Setup Time, HIGH or LOW D_n to LE	5.0	1.5	4.0	4.5	ns
t_h	Hold Time, HIGH or LOW D_n to LE	5.0	−2.0	0	0	ns
t_w	LE Pulse Width, HIGH	5.0	2.0	3.0	3.0	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	50.0	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

FAIRCHILD SEMICONDUCTOR™

August 1999
Revised October 1999

74ACT652
Transceiver/Register

General Description

The ACT652 consists of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to the HIGH logic level. Output Enable pins (OEAB, $\overline{\text{OEBA}}$) are provided to control the transceiver function.

Features

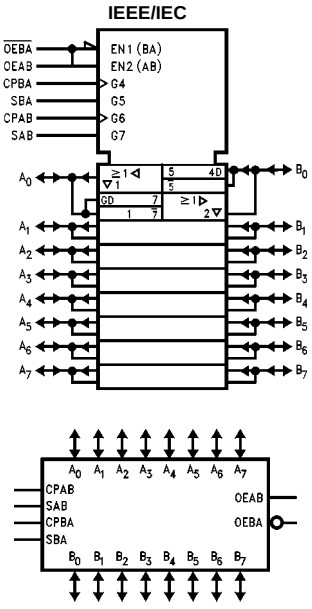
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

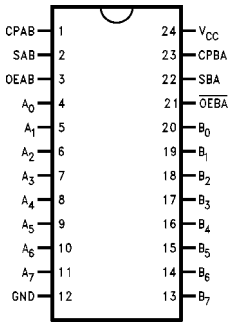
Order Number	Package Number	Package Description
74ACT652SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT652MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT652SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7, B_0–B_7	A and B Inputs/3-STATE Outputs
CPAB, CPBA	Clock Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{\text{OEBA}}$	Output Enable Inputs

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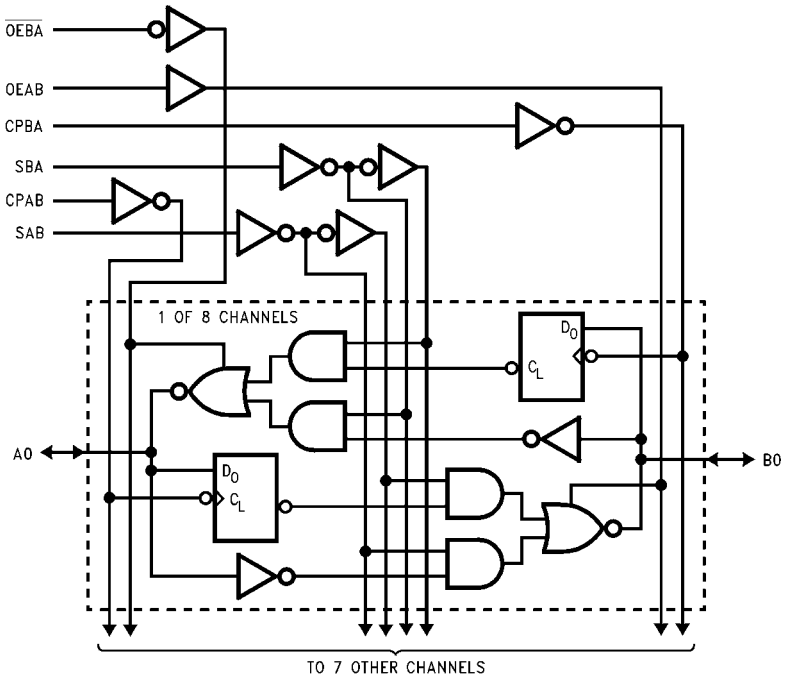
Function Table

Inputs						Inputs/Outputs (Note 1)		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

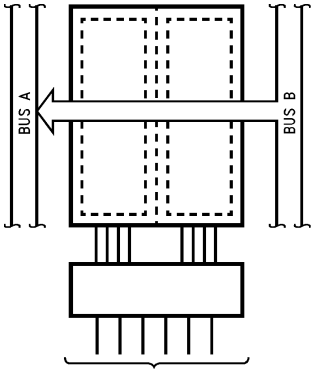
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in Figure 1 demonstrate the four fundamental bus-management functions that can be performed with the Octal bus transceivers and receivers.

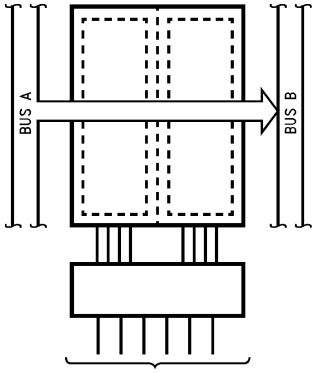
Data on the A or B data bus, or both can be stored in the internal D-type flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and $\overline{\text{OEBA}}$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Note A: Real-Time Transfer Bus B to Bus A



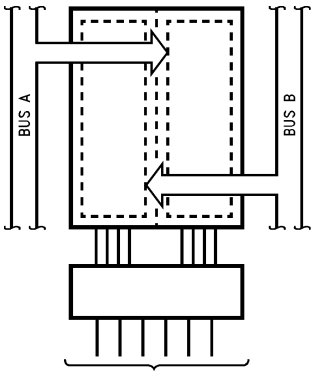
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Note B: Real-Time Transfer Bus A to Bus B



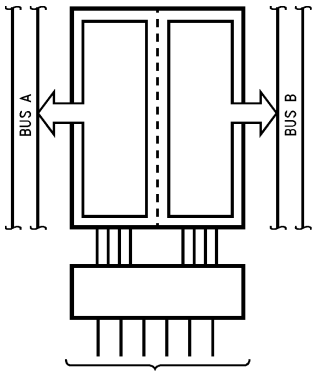
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

Note C: Storage



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
X	H	↓	X	X	X
L	X	X	↓	X	X
L	H	↓	↓	X	X

Note D: Transfer Storage Data to A or B



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

FIGURE 1.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 3)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZT}	Maximum I/O Leakage Current	5.5		± 0.6	± 6.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

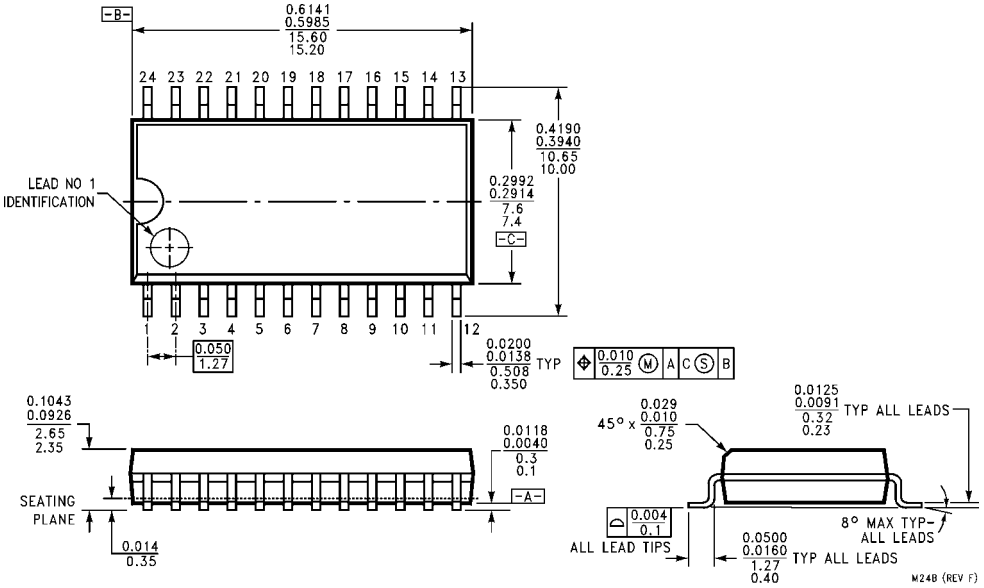
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Max. Clock Frequency	5.0						MHz
t_{PLH} t_{PHL}	Propagation Delay Clock to Bus	5.0	2.0	7.0	9.5	2.0	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay Bus to Bus	5.0	2.0	6.5	9.0	2.0	9.5	ns
t_{PLH} t_{PHL}	Propagation Delay SBA or SAB to A or B	5.0	2.5	6.5	10.0	2.5	10.5	ns
t_{PZH} t_{PZL}	Enable Time OEBA to A (Note 5)	5.0	2.0	7.0	10.5	2.0	11.0	ns
t_{PHZ} t_{PLZ}	Disable Time OEBA to A (Note 5)	5.0	1.0	5.0	8.0	1.0	8.5	
t_{PZH} t_{PZL}	Enable Time OEAB to B	5.0	2.0	7.0	10.5	2.0	11.0	
t_{PHZ} t_{PLZ}	Disable Time OEAB to B	5.0	1.0	5.0	8.0	1.0	8.5	ns
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW, Bus to Clock	5.0	3.0			3.0		ns
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW, Bus to Clock	5.0	1.5			1.5		ns
$t_w(H)$ $t_w(L)$	Clock Pulse Width HIGH or LOW	5.0	4.0			4.0		ns

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

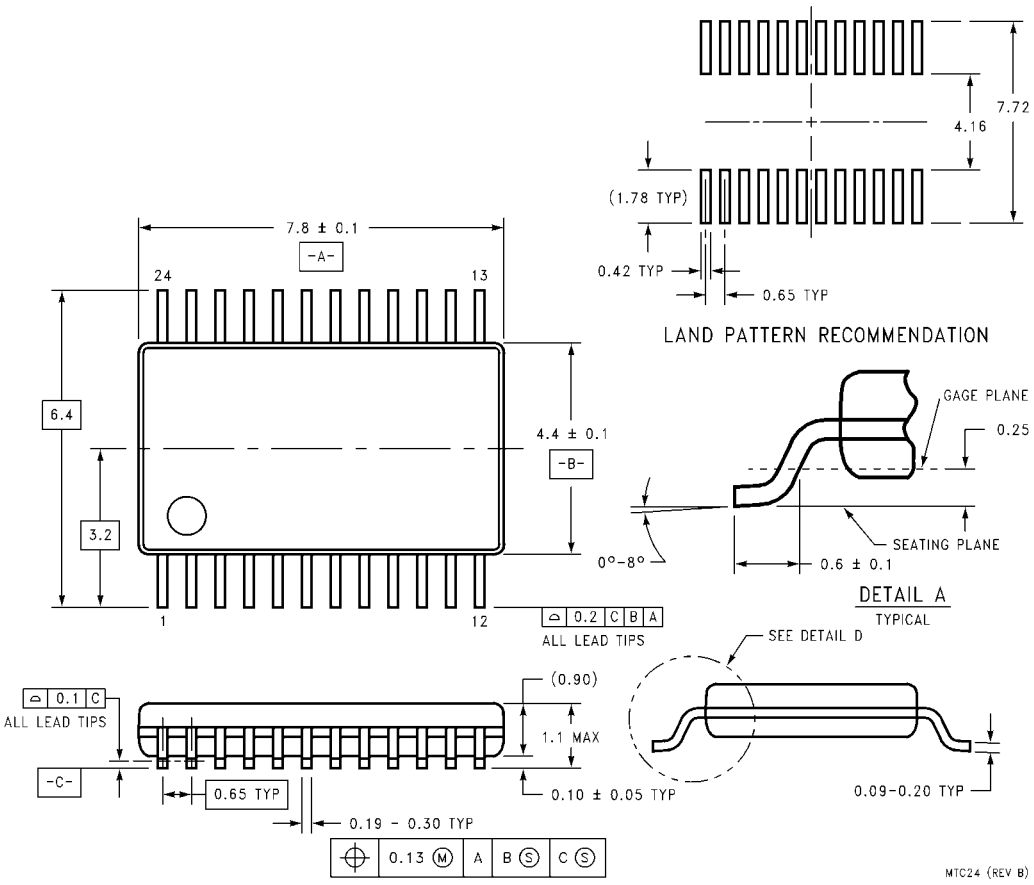
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	54	pF	$V_{CC} = 5.0V$

Physical Dimensions inches (millimeters) unless otherwise noted



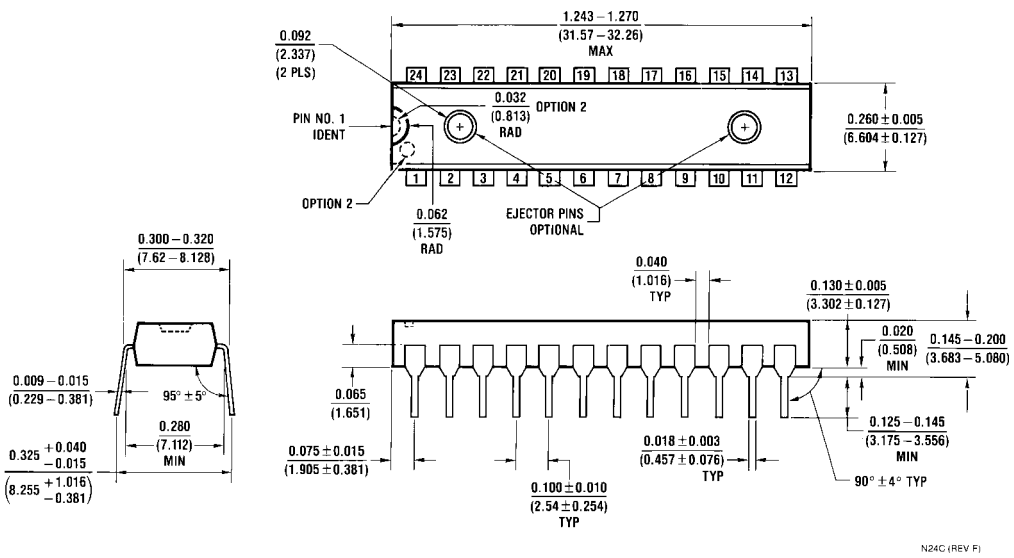
24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised December 1998

74ACT715•74ACT715-R
Programmable Video Sync Generator

General Description

The ACT715 and ACT715-R are 20-pin TTL-input compatible devices capable of generating Horizontal, Vertical and Composite Sync and Blank signals for televisions and monitors. All pulse widths are completely definable by the user. The devices are capable of generating signals for both interlaced and noninterlaced modes of operation. Equalization and serration pulses can be introduced into the Composite Sync signal when needed.

Four additional signals can also be made available when Composite Sync or Blank are used. These signals can be used to generate horizontal or vertical gating pulses, cursor position or vertical Interrupt signal.

These devices make no assumptions concerning the system architecture. Line rate and field/frame rate are all a function of the values programmed into the data registers, the status register, and the input clock frequency.

The ACT715 is mask programmed to default to a Clock Disable state. Bit 10 of the Status Register, Register 0, defaults to a logic "0". This facilitates (re)programming before operation.

The ACT715-R is the same as the ACT715 in all respects except that the ACT715-R is mask programmed to default to a Clock Enabled state. Bit 10 of the Status Register defaults to a logic "1". Although completely (re)programmable, the ACT715-R version is better suited for applications using the default 14.31818 MHz RS-170 register values. This feature allows power-up directly into operation, following a single CLEAR pulse.

Features

- Maximum Input Clock Frequency > 130 MHz
- Interlaced and non-interlaced formats available
- Separate or composite horizontal and vertical Sync and Blank signals available
- Complete control of pulse width via register programming
- All inputs are TTL compatible
- 8 mA drive on all outputs
- Default RS170/NTSC values mask programmed into registers
- ACT715-R is mask programmed to default to a Clock Enable state for easier start-up into 14.31818 MHz RS170 timing

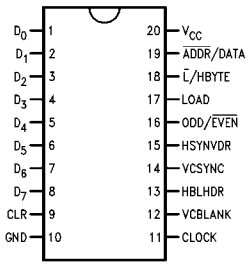
Ordering Code:

Order Number	Package Number	Package Description
74ACT715SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74ACT715PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT715-RSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74ACT715-RPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for DIP and SOIC



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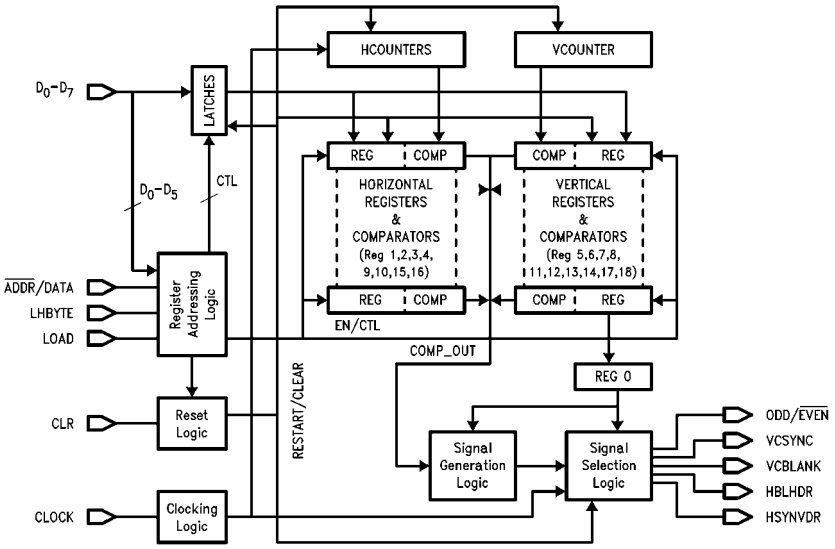
Logic Block Diagram



Pin Description

There are a Total of 13 inputs and 5 outputs on the ACT715.

Data Inputs D0–D7: The Data Input pins connect to the Address Register and the Data Input Register.

ADDR/DATA: The ADDR/DATA signal is latched into the device on the falling edge of the LOAD signal. The signal determines if an address (0) or data (1) is present on the data bus.

L/HBYTE: The L/HBYTE signal is latched into the device on the falling edge of the LOAD signal. The signal determines if data will be read into the 8 LSB's (0) or the 4 MSB's (1) of the Data Registers. A 1 on this pin when an ADDR/DATA is a 0 enables Auto-Load Mode.

LOAD: The LOAD control pin loads data into the Address or Data Registers on the rising edge. ADDR/DATA and L/HBYTE data is loaded into the device on the falling edge of the LOAD. The LOAD pin has been implemented as a Schmitt trigger input for better noise immunity.

CLOCK: System CLOCK input from which all timing is derived. The clock pin has been implemented as a Schmitt trigger for better noise immunity. The CLOCK and the LOAD signal are asynchronous and independent. Output state changes occur on the falling edge of CLOCK.

CLR: The CLEAR pin is an asynchronous input that initializes the device when it is HIGH. Initialization consists of setting all registers to their mask programmed values, and initializing all counters, comparators and registers. The CLEAR pin has been implemented as a Schmitt trigger for better noise immunity. A CLEAR pulse should be asserted by the user immediately after power-up to ensure proper initialization of the registers—even if the user plans to (re)program the device.

Note: A CLEAR pulse will disable the CLOCK on the ACT715 and will enable the CLOCK on the ACT715-R.

ODD/EVEN: Output that identifies if display is in odd (HIGH) or even (LOW) field of interlace when device is in interlaced mode of operation. In noninterlaced mode of operation this output is always HIGH. Data can be serially scanned out on this pin during Scan Mode.

VCSYNC: Outputs Vertical or Composite Sync signal based on value of the Status Register. Equalization and Serration pulses will (if enabled) be output on the VCSYNC signal in composite mode only.

VCBLANK: Outputs Vertical or Composite Blanking signal based on value of the Status Register.

HBLHDR: Outputs Horizontal Blanking signal, Horizontal Gating signal or Cursor Position based on value of the Status Register.

HSYNVDR: Outputs Horizontal Sync signal, Vertical Gating signal or Vertical Interrupt signal based on value of Status Register.

Register Description

All of the data registers are 12 bits wide. Width's of all pulses are defined by specifying the start count and end count of all pulses. Horizontal pulses are specified with-respect-to the number of clock pulses per line and vertical pulses are specified with-respect-to the number of lines per frame.

REG0—STATUS REGISTER

The Status Register controls the mode of operation, the signals that are output and the polarity of these outputs. The default value for the Status Register is 0 (000 Hex) for the ACT715 and is "1024" (400 Hex) for the ACT715-R.

Bits 0–2

B_2	B_1	B_0	VCBLANK	VCSYNC	HBLHDR	HSYNVDR
0	0	0	CBLANK	CSYNC	HGATE	VGATE
(DEFAULT)						
0	0	1	VBLANK	CSYNC	HBLANK	VGATE
0	1	0	CBLANK	VSYNC	HGATE	HSYNC
0	1	1	VBLANK	VSYNC	HBLANK	HSYNC
1	0	0	CBLANK	CSYNC	CUSOR	VINT
1	0	1	VBLANK	CSYNC	HBLANK	VINT
1	1	0	CBLANK	VSYNC	CUSOR	HSYNC
1	1	1	VBLANK	VSYNC	HBLANK	HSYNC

Bits 3–4

B_4	B_3	Mode of Operation
0	0	Interlaced Double Serration and Equalization (DEFAULT)
0	1	Non Interlaced Double Serration
1	0	Illegal State
1	1	Non Interlaced Single Serration and Equalization

Double Equalization and Serration mode will output equalization and serration pulses at twice the HSYNC frequency (i.e., 2 equalization or serration pulses for every HSYNC pulse). Single Equalization and Serration mode will output an equalization or serration pulse for every HSYNC pulse. In Interlaced mode equalization and serration pulses will be output during the VBLANK period of every odd and even field. Interlaced Single Equalization and Serration mode is not possible with this part.

Bits 5–8

Bits 5 through 8 control the polarity of the outputs. A value of zero in these bit locations indicates an output pulse active LOW. A value of 1 indicates an active HIGH pulse.

B5— VCBLANK Polarity

B6— VCSYNC Polarity

B7— HBLHDR Polarity

B8— HSYNVDR Polarity

Bits 9–11

Bits 9 through 11 enable several different features of the device.

B9— Enable Equalization/Serration Pulses (0)
Disable Equalization/Serration Pulses (1)

B10— Disable System Clock (0)
Enable System Clock (1)
Default values for B10 are "0" in the ACT715 and "1" in the ACT715-R.

B11— Disable Counter Test Mode (0)
Enable Counter Test Mode (1)
This bit is not intended for the user but is for internal testing only.

HORIZONTAL INTERVAL REGISTERS

The Horizontal Interval Registers determine the number of clock cycles per line and the characteristics of the Horizontal Sync and Blank pulses.

REG1— Horizontal Front Porch

REG2— Horizontal Sync Pulse End Time

REG3— Horizontal Blanking Width

REG4— Horizontal Interval Width # of Clocks per Line

VERTICAL INTERVAL REGISTERS

The Vertical Interval Registers determine the number of lines per frame, and the characteristics of the Vertical Blank and Sync Pulses.

REG5— Vertical Front Porch

REG6— Vertical Sync Pulse End Time

REG7— Vertical Blanking Width

REG8— Vertical Interval Width # of Lines per Frame

EQUALIZATION AND SERRATION PULSE SPECIFICATION REGISTERS

These registers determine the width of equalization and serration pulses and the vertical interval over which they occur.

REG 9— Equalization Pulse Width End Time

REG10— Serration Pulse Width End Time

REG11— Equalization/Serration Pulse Vertical Interval Start Time

REG12— Equalization/Serration Pulse Vertical Interval End Time

VERTICAL INTERRUPT SPECIFICATION REGISTERS

These Registers determine the width of the Vertical Interrupt signal if used.

REG13— Vertical Interrupt Activate Time

REG14— Vertical Interrupt Deactivate Time

CURSOR LOCATION REGISTERS

These 4 registers determine the cursor position location, or they generate separate Horizontal and Vertical Gating signals.

REG15— Horizontal Cursor Position Start Time

REG16— Horizontal Cursor Position End Time

REG17— Vertical Cursor Position Start Time

REG18— Vertical Cursor Position End Time

Signal Specification

HORIZONTAL SYNC AND BLANK SPECIFICATIONS

All horizontal signals are defined by a start and end time. The start and end times are specified in number of clock cycles per line. The start of the horizontal line is considered pulse 1 not 0. All values of the horizontal timing registers are referenced to the falling edge of the Horizontal Blank signal (see Figure 1). Since the first CLOCK edge, CLOCK #1, causes the first falling edge of the Horizontal Blank reference pulse, edges referenced to this first Horizontal edge are n + 1 CLOCKs away, where "n" is the width of the timing in question. Registers 1, 2, and 3 are programmed in this manner. The horizontal counters start at 1 and count until HMAX. The value of HMAX must be divisible by 2. This limitation is imposed because during interlace operation this value is internally divided by 2 in order to generate serration and equalization pulses at 2 × the horizontal frequency. Horizontal signals will change on the falling edge of the CLOCK signal. Signal specifications are shown below.

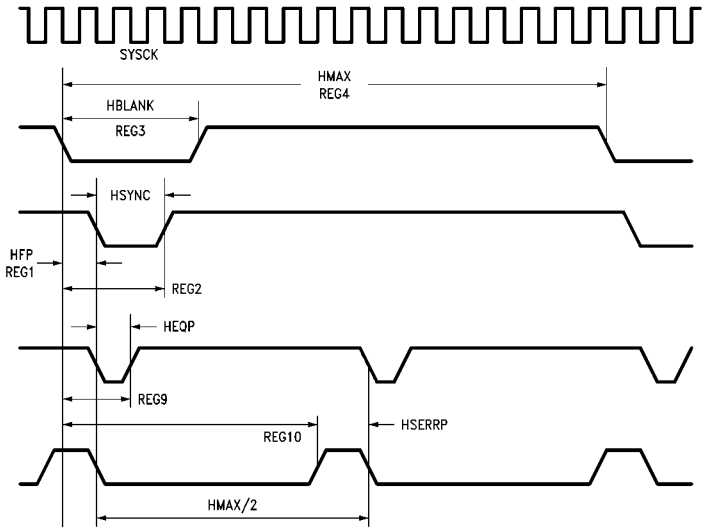


FIGURE 1. Horizontal Waveform Specification

Horizontal Period (HPER) = REG(4) × ckper

Horizontal Blanking Width: = [REG(3) − 1] × ckper

Horizontal Sync Width: = [REG(2) − REG(1)] × ckper

Horizontal Front Porch: = [REG(1) − 1] × ckper

VERTICAL SYNC AND BLANK SPECIFICATION

All vertical signals are defined in terms of number of lines per frame. This is true in both interlaced and noninterlaced modes of operation. Care must be taken to not specify the Vertical Registers in terms of lines per field. Since the first CLOCK edge, CLOCK #1, causes the first falling edge of the Vertical Blank (first Horizontal Blank) reference pulse, edges referenced to this first edge are n + 1 lines away, where "n" is the width of the timing in question. Registers 5, 6, and 7 are programmed in this manner. Also, in the interlaced mode, vertical timing is based on half-lines. Therefore registers 5, 6, and 7 must contain a value twice the total horizontal (odd and even) plus 1 (as described above). In non-interlaced mode, all vertical timing is based on whole-lines. Register 8 is always based on whole-lines and does not add 1 for the first clock. The vertical counter starts at the value of 1 and counts until the value of VMAX. No restrictions exist on the values placed in the vertical registers. Vertical Blank will change on the leading edge of HBLANK. Vertical Sync will change on the leading edge of HSYNC. (See Figure 2.) Vertical Frame Period (VPER) = REG(8) × hper

Vertical Field Period (VPER/n) = REG(8) × hper/n

Vertical Blanking Width = [REG(7) − 1] × hper/n

Vertical Syncing Width = [REG(6) − REG(5)] × hper/n

Vertical Front Porch = [REG(5) − 1] × hper/n

where n = 1 for noninterlaced

n = 2 for interlaced

COMPOSITE SYNC AND BLANK SPECIFICATION

Composite Sync and Blank signals are created by logically ANDing (ORing) the active LOW (HIGH) signals of the corresponding vertical and horizontal components of these signals. The Composite Sync signal may also include serration and/or equalization pulses. The Serration pulse interval occurs in place of the Vertical Sync interval. Equalization pulses occur preceding and/or following the Serration pulses. The width and location of these pulses can be programmed through the registers shown below. (See Figure 3.)

Horizontal Equalization PW = [REG(9) − REG(1)] × ckper

REG 9 = (HFP) + (HEQP) + 1

Horizontal Serration PW: = [REG(4)/n + REG(1) − REG(10)] × ckper

REG 10 = (HFP) + (HPER/2) − (HSERR) + 1

Where n = 1 for noninterlaced single serration/equalization

n = 2 for noninterlaced double serration/equalization

n = 2 for interlaced operation

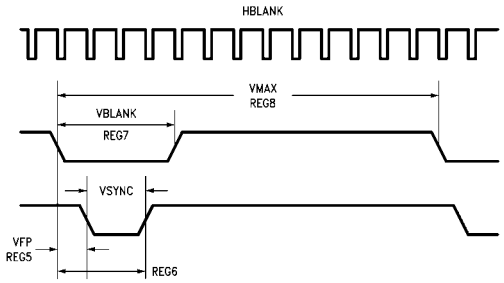


FIGURE 2. Vertical Waveform Specification

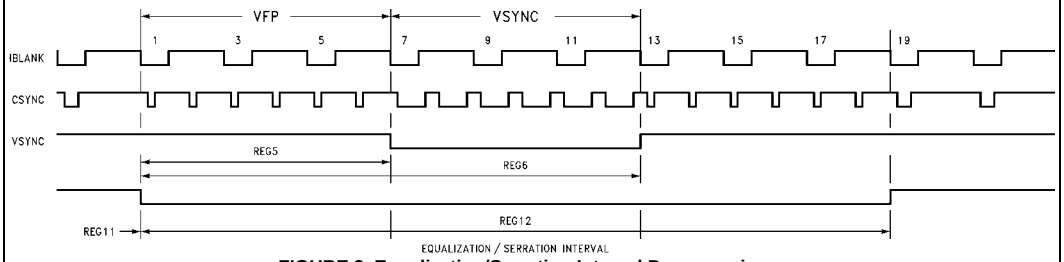


FIGURE 3. Equalization/Serration Interval Programming

HORIZONTAL AND VERTICAL GATING SIGNALS

Horizontal Drive and Vertical Drive outputs can be utilized as general purpose Gating Signals. Horizontal and Vertical Gating Signals are available for use when Composite Sync and Blank signals are selected and the value of Bit 2 of the Status Register is 0. The Vertical Gating signal will change in the same manner as that specified for the Vertical Blank.

Horizontal Gating Signal Width = [REG(16) − REG(15)] × ckper

Vertical Gating Signal Width: = [REG(18) − REG(17)] × hper

CURSOR POSITION AND VERTICAL INTERRUPT

The Cursor Position and Vertical Interrupt signal are available when Composite Sync and Blank signals are selected and Bit 2 of the Status Register is set to the value of 1. The Cursor Position generates a single pulse of n clocks wide during every line that the cursor is specified. The signals are generated by logically ORing (ANDing) the active LOW (HIGH) signals specified by the registers used for generating Horizontal and Vertical Gating signals. The Vertical Interrupt signal generates a pulse during the vertical interval specified. The Vertical Interrupt signal will change in the same manner as that specified for the Vertical Blanking signal.

Horizontal Cursor Width = [REG(16) − REG(15)] × ckper

Vertical Cursor Width = [REG(18) − REG(17)] × hper

Vertical Interrupt Width = [REG(14) − REG(13)] × hper

Addressing Logic

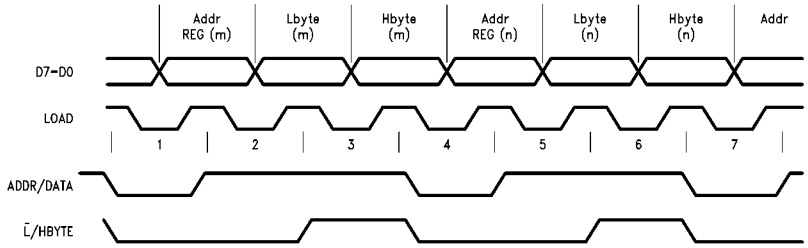
The register addressing logic is composed of two blocks of logic. The first is the address register and counter (ADDRCNTR), and the second is the address decode (ADDRDEC).

ADDRCNTR LOGIC

Addresses for the data registers can be generated by one of two methods. Manual addressing requires that each byte of each register that needs to be loaded needs to be addressed. To load both bytes of all 19 registers would require a total of 57 load cycles (19 address and 38 data cycles). Auto Addressing requires that only the initial register value be specified. The Auto Load sequence would require only 39 load cycles to completely program all registers (1 address and 38 data cycles). In the auto load sequence the low order byte of the data register will be written first followed by the high order byte on the next load cycle. At the time the High Byte is written the address counter is incremented by 1. The counter has been implemented to loop on the initial value loaded into the address register. For example: If a value of 0 was written into the address register then the counter would count from 0 to 18 before resetting back to 0. If a value of 15 was written into the address register then the counter would count from 15 to 18 before looping back to 15. If a value greater than or equal to 18 is placed into the address register the counter will continuously loop on this value. Auto addressing is initiated on the falling edge of LOAD when ADDRDATA is 0 and LHBYTE is 1. Incrementing and loading of data registers will not commence until the falling edge of LOAD after ADDRDATA goes to 1. The next rising edge of LOAD will load the first byte of data. Auto Incrementing is disabled on the falling edge of LOAD after ADDRDATA and LHBYTE goes low.

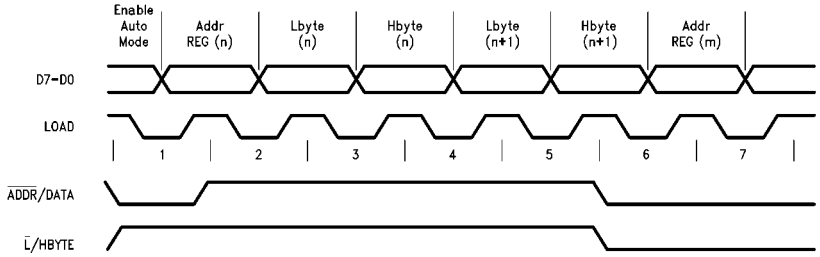
Manual Addressing Mode

Cycle #	Load Falling Edge	Load Rising Edge
1	Enable Manual Addressing	Load Address m
2	Enable Lbyte Data Load	Load Lbyte m
3	Enable Hbyte Data Load	Load Hbyte m
4	Enable Manual Addressing	Load Address n
5	Enable Lbyte Data Load	Load Lbyte n
6	Enable Hbyte Data Load	Load Hbyte n



Auto Addressing Mode

Cycle #	Load Falling Edge	Load Rising Edge
1	Enable Auto Addressing	Load Start Address n
2	Enable Lbyte Data Load	Load Lbyte (n)
3	Enable Hbyte Data Load	Load Hbyte (n); Inc Counter
4	Enable Lbyte Data Load	Load Lbyte (n+1)
5	Enable Hbyte Data Load	Load Hbyte (n+1); Inc Counter
6	Enable Manual Addressing	Load Address



ADDRDEC LOGIC

The ADDRDEC logic decodes the current address and generates the enable signal for the appropriate register. The enable values for the registers and counters change on the falling edge of LOAD. Two types of ADDRDEC logic is enabled by 2 pair of addresses, Addresses 22 or 54 (Vectored Restart logic) and Addresses 23 or 55 (Vectored Clear logic). Loading these addresses will enable the appropriate logic and put the part into either a Restart (all counter registers are reinitialized with preprogrammed data) or Clear (all registers are cleared to zero) state. Reloading the same ADDRDEC address will not cause any change in the state of the part. The outputs during these states are frozen and the internal CLOCK is disabled. Clocking the part during a Vectored Restart or Vectored Clear state will have no effect on the part. To resume operation in the new state, or disable the Vectored Restart or Vectored Clear state, another non-ADDRDEC address must be loaded. Operation will begin in the new state on the rising edge of the non-ADDRDEC load pulse. It is recommended that an unused address be loaded following an ADDRDEC operation to prevent data registers from accidentally being corrupted. The following Addresses are used by the device.

Address 0 Status Register REG0

Address 1–18 Data Registers REG1–REG18

Address 19–21 Unused

Address 22/54 Restart Vector (Restarts Device)

Address 23/55 Clear Vector (Zeros All Registers)

Address 24–31 Unused

Address 32–50 Register Scan Addresses

Address 51–53 Counter Scan Addresses

Address 56–63 Unused

At any given time only one register at most is selected. It is possible to have no registers selected.

VECTORED RESTART ADDRESS

The function of addresses 22 (16H) or 54 (36H) are similar to that of the CLR pin except that the preprogramming of the registers is not affected. It is recommended but not required that this address is read after the initial device configuration load sequence. A 1 on the ADDRDATA pin (Auto Addressing Mode) will not cause this address to automatically increment. The address will loop back onto itself regardless of the state of ADDRDATA unless the address on the Data inputs has been changed with ADDRDATA at 0.

VECTORED CLEAR ADDRESS

Addresses 23 (17H) or 55 (37H) is used to clear all registers to zero simultaneously. This function may be desirable to use prior to loading new data into the Data or Status Registers. This address is read into the device in a similar fashion as all of the other registers. A 1 on the ADDRDATA pin (Auto Addressing Mode) will not cause this address to automatically increment. The address will loop back onto itself regardless of the state of ADDRDATA unless the address on the Data inputs has been changed with ADDRDATA at 0.

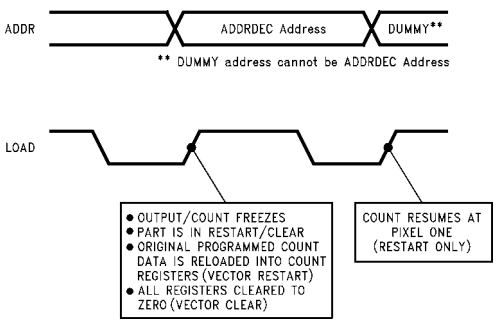


FIGURE 4. ADDRDEC Timing

GEN LOCKING

The ACT715 and ACT715-R is designed for master SYNC and BLANK signal generation. However, the devices can be synchronized (slaved) to an external timing signal in a limited sense. Using Vectored Restart, the user can reset the counting sequence to a given location, the beginning, at a given time, the rising edge of the LOAD that removes Vector Restart. At this time the next CLOCK pulse will be CLOCK 1 and the count will restart at the beginning of the first odd line.

Preconditioning the part during normal operation, before the desired synchronizing pulse, is necessary. However, since LOAD and CLOCK are asynchronous and independent, this is possible without interruption or data and performance corruption. If the defaulted 14.31818 MHz RS-170 values are being used, preconditioning and restarting can be minimized by using the CLEAR pulse instead of the Vectored Restart operation. The ACT715-R is better suited for this application because it eliminates the need to program a 1 into Bit 10 of the Status Register to enable the CLOCK. Gen Locking to another count location other than the very beginning or separate horizontal/vertical resetting is not possible with the ACT715 nor the ACT715-R.

SCAN MODE LOGIC

A scan mode is available in the ACT715 that allows the user to non-destructively verify the contents of the registers. Scan mode is invoked through reading a scan address into the address register. The scan address of a given register is defined by the Data register address + 32. The internal Clocking signal is disabled when a scan address is read. Disabling the clock freezes the device in it's present state. Data can then be serially scanned out of the data registers through the ODD/EVEN Pin. The LSB will be scanned out first. Since each register is 12 bits wide, completely scanning out data of the addressed register will require 12 CLOCK pulses. More than 12 CLOCK pulses on the same register will only cause the MSB to repeat on the output. Re-scanning the same register will require that register to be reloaded. The value of the two horizontal counters and 1 vertical counter can also be scanned out by using address numbers 51–53. Note that before the part will scan out the data, the LOAD signal must be brought back HIGH.

Normal device operation can be resumed by loading in a non-scan address. As the scanning of the registers is a non-destructive scan, the device will resume correct operation from the point at which it was halted.

RS170 Default Register Values

The tables below show the values programmed for the RS170 Format (using a 14.31818 MHz clock signal) and how they compare against the actual EIA RS170 Specifications. The default signals that will be output are CSYNC, CBLANK, HDRIVE and VDRIVE. The device initially starts at the beginning of the odd field of interlace. All signals have active low pulses and the clock is disabled at power up. Registers 13 and 14 are not involved in the actual signal information. If the Vertical Interrupt was selected so that a pulse indicating the active lines would be output.

Reg	D Value	H	Register Description
REG0	0	000	Status Register (715)
REG0	1024	400	Status Register (715-R)
REG1	23	017	HFP End Time
REG2	91	05B	HSYNC Pulse End Time
REG3	157	09D	HBLANK Pulse End Time
REG4	910	38E	Total Horizontal Clocks
REG5	7	007	VFP End Time
REG6	13	00D	VSYNC Pulse End Time
REG7	41	029	VBLANK Pulse End Time
REG8	525	20D	Total Vertical Lines
REG9	57	039	Equalization Pulse End Time
REG10	410	19A	Serration Pulse Start Time
REG11	1	001	Pulse Interval Start Time
REG12	19	013	Pulse Interval End Time
REG13	41	029	Vertical Interrupt Activate Time
REG14	526	20E	Vertical Interrupt Deactivate Time
REG15	911	38F	Horizontal Drive Start Time
REG16	92	05C	Horizontal Drive End Time
REG17	1	001	Vertical Drive Start Time
REG18	21	015	Vertical Drive End Time

	Rate	Period
Input Clock	14.31818 MHz	69.841 ns
Line Rate	15.73426 kHz	63.556 µs
Field Rate	59.94 Hz	16.683 ms
Frame Rate	29.97 Hz	33.367 ms

RS170 Horizontal Data

Signal	Width	µs	%H	Specification (µs)
HFP	22 Clocks	1.536		1.5 ±0.1
HSYNC Width	68 Clocks	4.749	7.47	4.7 ±0.1
HBLANK Width	156 Clocks	10.895	17.15	10.9 ±0.2
HDRIVE Width	91 Clocks	6.356	10.00	0.1H ±0.005H
HEQP Width	34 Clocks	2.375	3.74	2.3 ±0.1
HSERR Width	68 Clocks	4.749	7.47	4.7 ±0.1
HPER iod	910 Clocks	63.556	100	

RS170 Vertical Data

VFP	3 Lines	190.67		6 EQP Pulses
VSYNC Width	3 Lines	190.67		6 Serration Pulses
VBLANK Width	20 Lines	1271.12	7.62	0.075V ± 0.005V
VDRIVE Width	11.0 Lines	699.12	4.20	0.04V ± 0.006V
VEQP Intrvl	9 Lines		3.63	9 Lines/Field
VPERiod (field)	262.5 Lines	16.683 ms		16.683 ms/Field
VPERiod (frame)	525 Lines	33.367 ms		33.367 ms/Frame

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source	
or Sink Current (I_O)	±15 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±20 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

For ACT Family Devices over Operating Temperature Range (unless otherwise specified)

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF		T_A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4	V	
		4.5		3.86	3.76	V	V_{IN} = V_{IL}/V_{IH}
		5.5		4.86	4.76	V	I_{OH} = −8 mA (Note 2)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1	V	
		4.5		0.36	0.44	V	V_{IN} = V_{IL}/V_{IH}
		5.5		0.36	0.44	V	I_{OH} = +8 mA (Note 2)
I_{OLD}	Minimum Dynamic	5.5			32.0	mA	V_{OLD} = 1.65V
	Output Current						
I_{OHD}	Minimum Dynamic	5.5			−32.0	mA	V_{OHD} = 3.85V
	Output Current						
I_{IN}	Maximum Input	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
	Leakage Current						
I_{CC}	Supply Current	5.5		8.0	80	μA	V_{IN} = V_{CC}, GND
	Quiescent						
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_{IN} = V_{CC} − 2.1V

Note 2: All outputs loaded; thresholds on input associated with input under test.

Note 3: Test Load 50 pF, 500Ω to Ground.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAXI}	Interlaced f_{max} (HMAX/2 is ODD)	5.0	170	190		150		MHz
f_{max}	Non-Interlaced f_{max} (HMAX/2 is EVEN)	5.0	190	220		175		MHz
t_{PLH1} t_{PHL1}	Clock to Any Output	5.0	4.0	13.0	15.5	3.5	18.5	ns
t_{PLH2} t_{PHL2}	Clock to ODDEVEN (Scan Mode)	5.0	4.5	15.0	17.0	3.5	20.5	ns
t_{PLH3}	Load to Outputs	5.0	4.0	11.5	16.0	3.0	19.5	ns

AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$	Units
			Typ	Guaranteed Minimums	
	Control Setup Time				
t_{sc}	ADDR/DATA to LOAD–	5.0	3.0	4.0	4.5	ns
t_{sc}	L/HBYTE to LOAD–		3.0	4.0	4.5	ns
	Data Setup Time					
t_{sd}	D7–D0 to LOAD+	5.0	2.0	4.0	4.5	ns
	Control Hold Time					
t_{hc}	LOAD– to ADDR/DATA	5.0	0	1.0	1.0	ns
	LOAD– to L/HBYTE		0	1.0	1.0	ns
	Data Hold Time					
t_{hd}	LOAD+ to D7–D0	5.0	1.0	2.0	2.0	ns
t_{rec}	LOAD+ to CLK (Note 4)	5.0	5.5	7.0	8.0	ns
	Load Pulse Width					
t_{wld-}	LOW	5.0	3.0	5.5	5.5	ns
t_{wld+}	HIGH	5.0	3.0	5.0	7.5	ns
t_{wclr}	CLR Pulse Width HIGH	5.0	5.5	6.5	9.5	ns
t_{wck}	CLOCK Pulse Width (HIGH or LOW)	5.0	2.5	3.0	3.5	ns

Note 4: Removal of Vectored Reset or Restart to Clock.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	7.0	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	17.0	pF	$V_{CC} = 5.0V$

Capacitance (Continued)

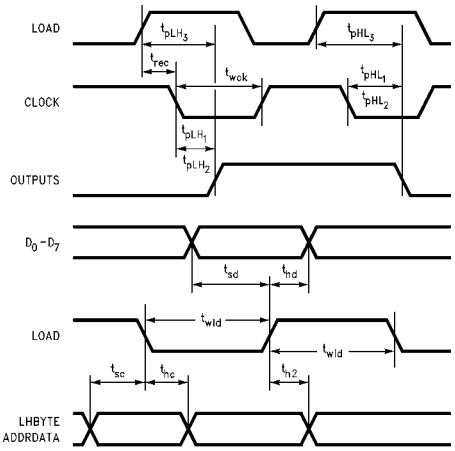


FIGURE 5. AC Specifications

Additional Applications Information

POWERING UP

The ACT715 default value for Bit 10 of the Status Register is 0. This means that when the CLEAR pulse is applied and the registers are initialized by loading the default values the CLOCK is disabled. Before operation can begin, Bit 10 must be changed to a 1 to enable CLOCK. If the default values are needed (no other programming is required) then Figure 6 illustrates a hardwired solution to facilitate the enabling of the CLOCK after power-up. Should control signals be difficult to obtain, Figure 7 illustrates a possible solution to automatically enable the CLOCK upon power-up. Use of the ACT715-R eliminates the need for most of this circuitry. Modifications of the Figure 7 circuit can be made to obtain the lone CLEAR pulse still needed upon power-up.

Note that, although during a Vectored Restart none of the preprogrammed registers are affected, some signals are affected for the duration of one frame only. These signals are the Horizontal and Vertical Drive signals. After a Vectored Restart the beginning of these signals will occur at the first CLK. The end of the signals will occur as programmed. At the completion of the first frame, the signals will resume to their programmed start and end time.

PREPROGRAMMING "ON-THE-FLY"

Although the ACT715 and ACT715-R are completely programmable, certain limitations must be set as to when and how the parts can be reprogrammed. Care must be taken when reprogramming any End Time registers to a new value that is lower than the current value. Should the reprogramming occur when the counters are at a count after the new value but before the old value, then the counters will continue to count up to 4096 before rolling over.

For this reason one of the following two precautions are recommended when reprogramming "on-the-fly". The first recommendation is to reprogram horizontal values during the horizontal blank interval only and/or vertical values during the vertical blank interval only. Since this would require delicate timing requirements the second recommendation may be more appropriate.

The second recommendation is to program a Vectored Restart as the final step of reprogramming. This will ensure that all registers are set to the newly programmed values and that all counters restart at the first CLK position. This will avoid overrunning the counter end times and will maintain the video integrity.

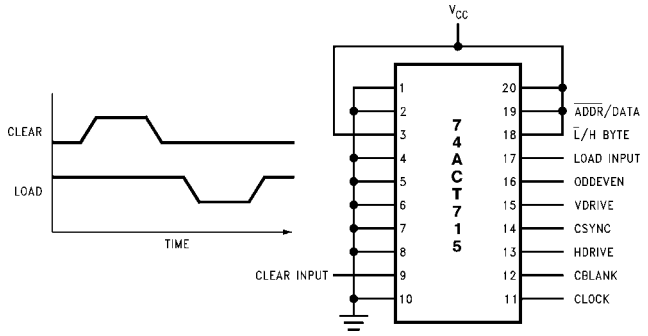
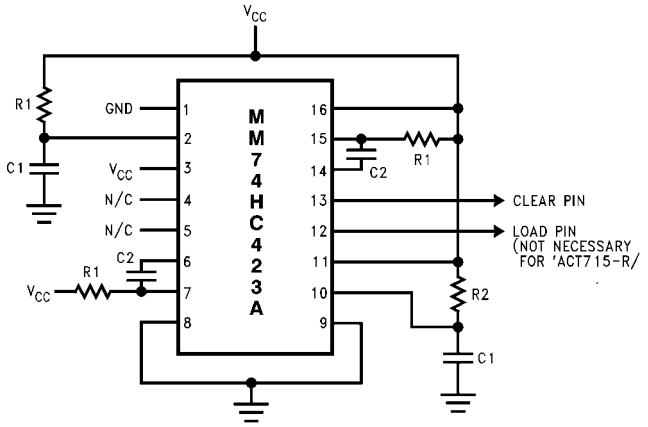


FIGURE 6. Default RS170 Hardwire Configuration



Note: A 74HC221A may be substituted for the 74HC423A Pin 6 and Pin 14 must be hardwired to GND

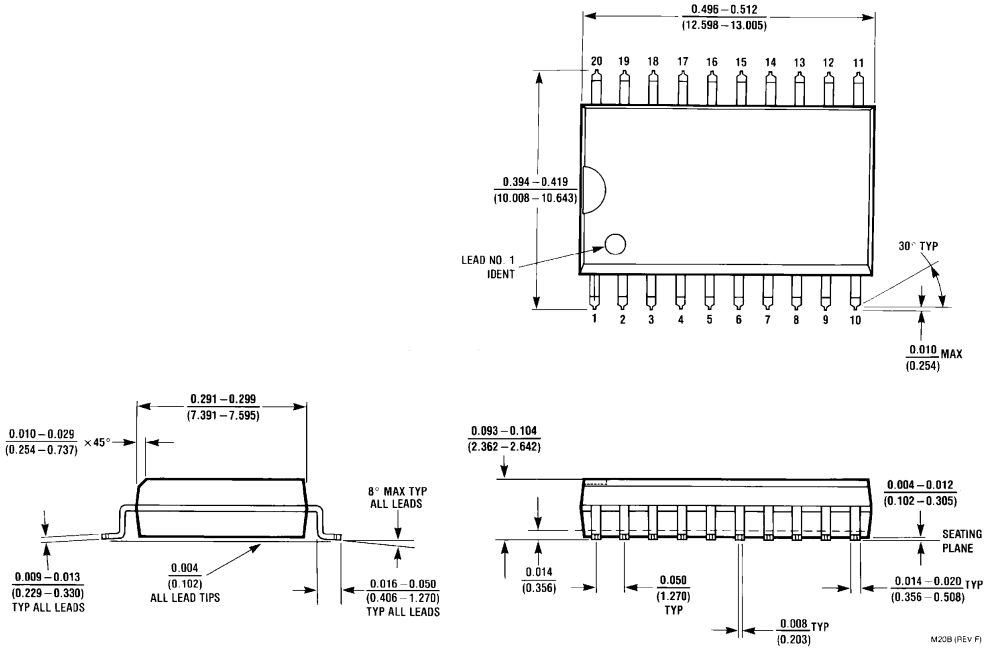
Components

R1: 4.7k C1: 10 µF

R2:10k C2: 50 pF

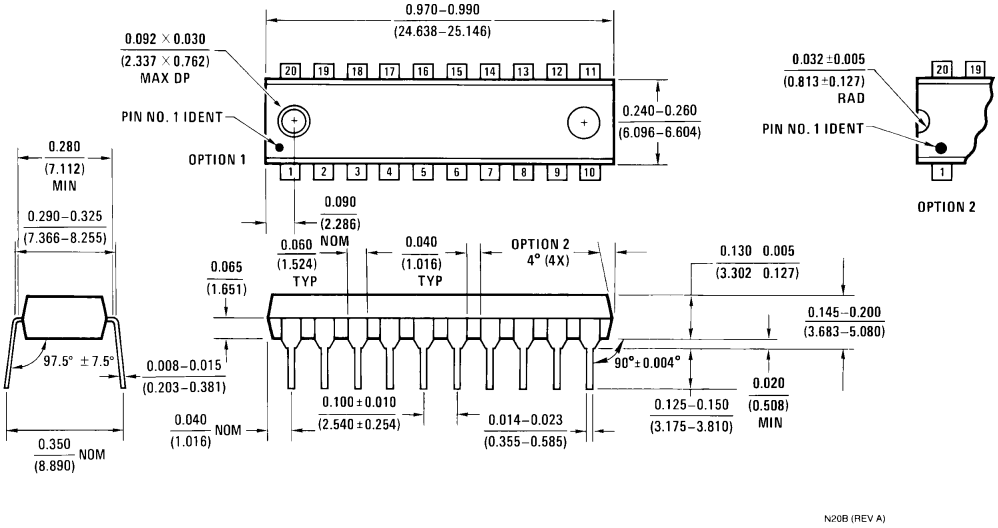
FIGURE 7. Circuit for Clear and Load Pulse Generation

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number N20A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1988
Revised January 1999

74ACT818
8-Bit Diagnostic Register

General Description

The ACT818 is a high-speed, general-purpose pipeline register with an on-board diagnostic register for performing serial diagnostics and/or writable control store loading.

The D-to-Y path provides an 8-bit parallel data path pipeline register for normal system operation. The diagnostic register can load parallel data to or from the pipeline register and can output data through the D input port (as in WCS loading).

The 8-bit diagnostic register has multiplexer inputs that select parallel inputs from the Y-port or adjacent bits in the diagnostic register to operate as a right-shift-only register. This register can then participate in a serial loop throughout the system where normal data, address, status and control registers are replaced with ACT818 diagnostic pipeline registers. The loop can be used to scan in a complete test routine starting point (Data, Address, etc.). Then after a specified number of machine cycles it scans out the results to be inspected for the expected results. WCS loading can be accomplished using the same technique. An instruction word can be serially shifted into the shadow register and written into the WCS RAM by enabling the D output.

Features

- On-line and off-line system diagnostics
- Swaps the contents of diagnostic register and output register
- Diagnostic register and diagnostic testing
- Cascadable for wide control words as used in microprogramming
- Edge-triggered D registers
- Outputs source/sink 24 mA
- ACT818 has TTL-compatible inputs
- ACT818 is functionally- and pin-compatible to AMD Am29818 and MMI 74S818

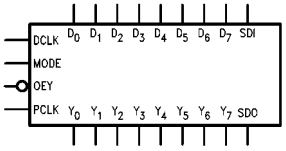
Applications

- Register for microprogram control store
- Status register
- Data register
- Instruction register
- Interrupt mask register
- Pipeline register
- General purpose register
- Parallel-serial/serial-parallel converter

Ordering Code:

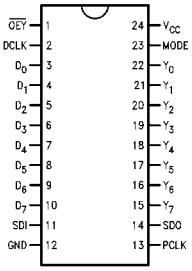
Order Number	Order Package	Package Description
74ACT818SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Logic Symbol



Connection Diagram

Pin Assignment for DIP



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Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
SDI	Serial Data Input
DCLK	Diagnostics Clock
MODE	Control Input
PCLK	Pipeline Register Clock
$\overline{OEY}$	Output Enable Input
SDO	Serial Data Output
Y_0–Y_7	Data Outputs

Functional Description

Data transfers into the diagnostic register occur on the LOW-to-HIGH transition of DCLK. Mode and SDI determine what data source will be loaded. The pipeline register is loaded on the LOW-to-HIGH transition of PCLK. Mode selects whether the data source is the data input or the diagnostic register output. Because of the independence of the clock inputs, data can be shifted in the diagnostic register via DCLK and loaded into the pipeline register from the data input via PCLK simultaneously, as long as no setup or hold times are violated. This simultaneous operation is legal.

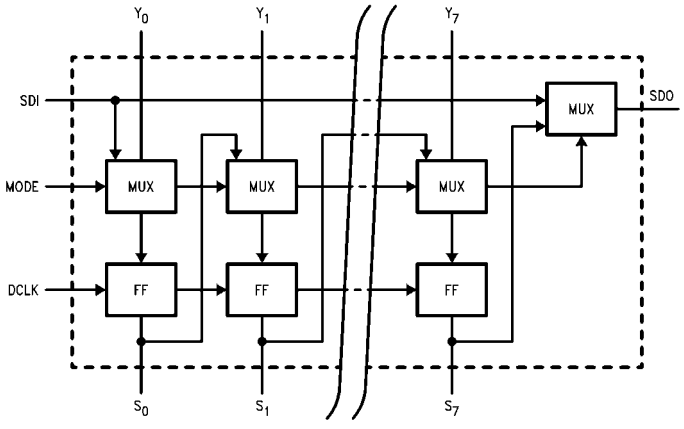
Function Table

Inputs				Outputs			Operation
SDI	MODE	DCLK	PCLK	SDO	Diagnostic Reg.	Pipeline Reg.	
X	L	⌐	X	S7	SI<SI – 1, SO<SD_I	NA	Serial Shift; D_7–D_0 Disabled
X	L	X	⌐	S7	NA	PI<DI	Normal Load Pipeline Register
L	H	⌐	X	L	SI<YI	NA	Load Diagnostic Register from Y; DI Disabled
X	H	X	⌐	SDI	NA	PI<SI	Load Pipeline Register from Diagnostic Register
H	H	⌐	X	H	Hold	NA	Hold Diagnostic Register; DI Enabled

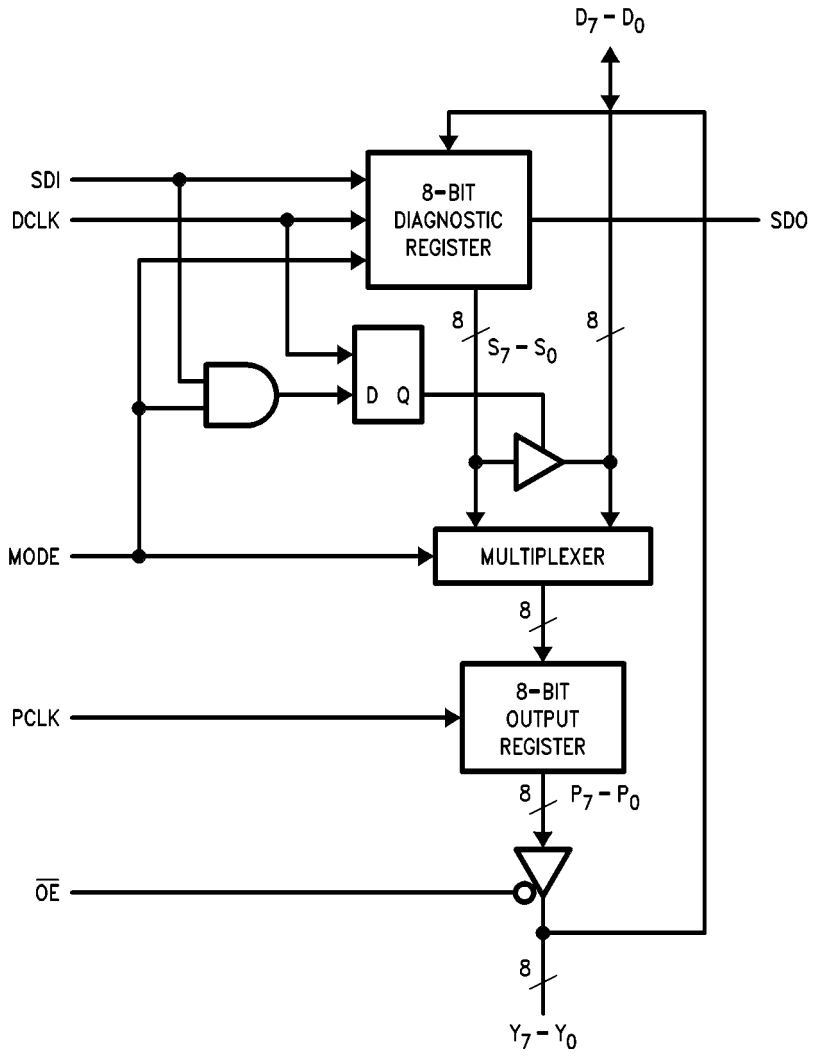
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

⌐ = LOW-to-HIGH Clock Transition

Diagnostic Register



Block Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8		V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
I_{IN}	Maximum Input	5.5		± 0.1	± 1.0	µA	V_{IN} = V_{CC}
	Leakage Current						
I_{OZ}	Maximum 3-STATE	5.5		± 0.5	± 5.0	µA	$\overline{OE}$ = V_{IH}
	Leakage Current						V_{OUT} = 0V, V_{CC}
I_{CC}	Maximum Quiescent	5.5		8.0	80.0	µA	V_{IN} = V_{CC} or GND
	Supply Current						
I_{CCT}	Maximum Additional	5.5			1.5	mA	V_{IN} = V_{CC} − 2.1V
	I_{CC}/Input						V_{CC} = 5.5V
V_{OH}	Minimum HIGH						V_{IN} = V_{IL} or V_{IH}
	Level Output Voltage,	4.5		3.86	3.76	V	I_{OH} = −24 mA
	Y_0–Y_7 Outputs	5.5		4.86	4.76	V	I_{OH} = −24 mA (Note 2)
	Minimum HIGH						
	Level Output Voltage,	4.5		3.86	3.76	V	I_{OH} = −8 mA
	D_0–D_7, SDO Outputs	5.5		4.86	4.76	V	I_{OH} = −8 mA
V_{OL}	Maximum LOW						V_{IN} = V_{IL} or V_{IH}
	Level Output Voltage,	4.5		0.36	0.44	V	I_{OL} = 24 mA
	Y_0–Y_7 Outputs	5.5		0.36	0.44	V	I_{OL} = 24 mA (Note 2)
	Maximum LOW Level Output Voltage,	4.5		0.36	0.44	V	I_{OL} = 8 mA
	D_0–D_7, SDO Outputs	5.5		0.36	0.44	V	I_{OL} = 8 mA
I_{OLD}	Minimum Dynamic Output Current	5.5			75	mA	V_{OLD} = 1.65V Max
	Y_0–Y_7 Outputs						
I_{OHD}	Minimum Dynamic Output Current	5.5			−75	mA	V_{OHD} = 3.85V Min
	Y_0–Y_7 Outputs						

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$		$T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits			
I_{OLD}	Minimum Dynamic Output Current D_0–D_7, SDO Outputs (Note 3)	5.5			32	mA	V_{OLD} = 1.65V Max
I_{OHD}	Minimum Dynamic Output Current D_0–D_7, SDO Outputs (Note 3)	5.5			–32	mA	V_{OHD} = 3.85V Min

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Test load 50 pF, 500Ω to ground.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, C_L = 50 pF			$T_A = -40°C$ to $+85°C$, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay PCLK to Y	5.0	3.0	6.0	9.0	2.5	9.5	ns
t_{PLH}	Propagation Delay PCLK to Y	5.0	3.0	6.5	9.0	2.5	10.0	ns
t_{PHL}	Propagation Delay MODE to SDO	5.0	4.0	8.0	11.0	3.5	12.0	ns
t_{PLH}	Propagation Delay MODE to SDO	5.0	4.0	8.0	11.5	4.0	12.5	ns
t_{PHL}	Propagation Delay SDI to SDO	5.0	3.5	7.5	10.5	3.0	12.0	ns
t_{PLH}	Propagation Delay SDI to SDO	5.0	3.5	7.5	10.5	3.5	12.0	ns
t_{PHL}	Propagation Delay DCLK to SDO	5.0	4.5	9.0	12.5	4.0	14.0	ns
t_{PLH}	Propagation Delay DCLK to SDO	5.0	4.5	9.5	13.0	4.0	14.5	ns
t_{PZL}	Output Enable Time $\overline{OEY}$ to Y_n	5.0	2.5	6.0	9.0	2.5	10.0	ns
t_{PLZ}	Output Disable Time $\overline{OEY}$ to Y_n	5.0	1.5	5.5	8.0	1.0	9.0	ns
t_{PZL}	Output Enable Time DCLK to D_n	5.0	3.0	8.0	12.0	3.0	13.5	ns
t_{PLZ}	Output Disable Time DCLK to D_n	5.0	2.0	8.5	11.0	1.5	12.0	ns
t_{PZH}	Output Enable Time $\overline{OEY}$ to Y_n	5.0	3.0	8.0	10.0	2.5	11.0	ns
t_{PHZ}	Output Disable Time $\overline{OEY}$ to Y_n	5.0	2.5	9.0	11.0	2.0	11.5	ns
t_{PZH}	Output Enable Time DCLK to D_n	5.0	3.0	6.5	11.5	3.0	13.0	ns
t_{PHZ}	Output Disable Time DCLK to D_n	5.0	3.0	7.5	12.0	2.0	13.0	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V.

AC Operating Requirements

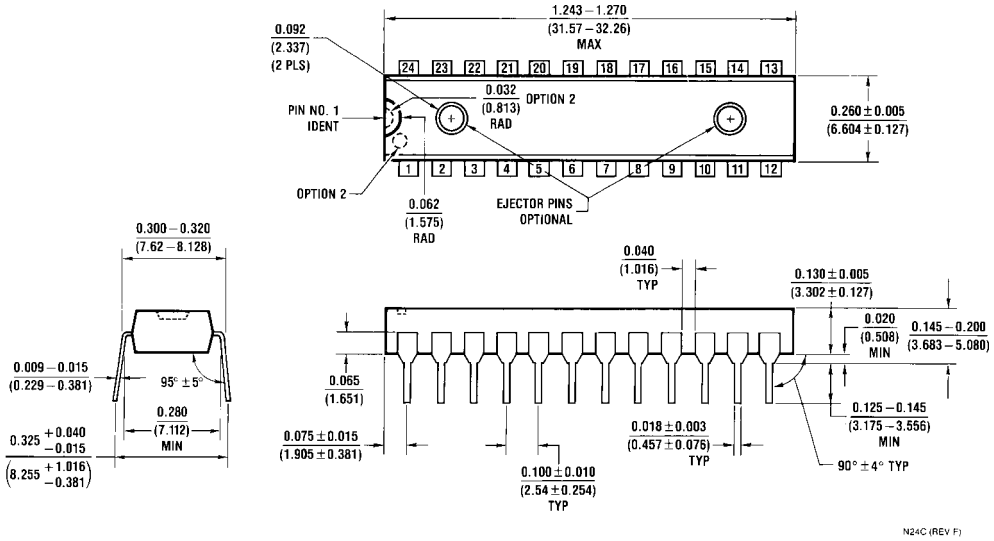
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time D to PCLK	5.0	1.0	4.0	5.0	ns
t_H	Hold Time D to PCLK	5.0	0.0	1.0	1.0	ns
t_H	Setup Time MODE to PCLK	5.0	2.5	4.5	5.5	ns
t_H	Hold Time MODE to PCLK	5.0	−1.0	0.0	0.0	ns
t_S	Setup Time Y to DCLK	5.0	0.5	2.5	2.5	ns
t_S	Hold Time Y to DCLK	5.0	0	1.0	1.5	ns
t_S	Setup Time MODE to DCLK	5.0	2.0	4.0	4.0	ns
t_H	Hold Time MODE to DCLK	5.0	−0.5	1.0	1.0	ns
t_S	Setup Time SDI to DCLK	5.0	2.0	3.5	4.5	ns
t_H	Hold Time SDI to DCLK	5.0	−0.5	1.0	1.0	ns
t_S	Setup Time DCLK to PCLK	5.0	6.0	9.0	10.5	ns
t_S	Setup Time PCLK to DCLK	5.0	6.0	11.0	11.5	ns
t_W	Pulse Width PCLK HIGH or LOW	5.0	2.0	3.0	3.0	ns
t_W	Pulse Width DCLK HIGH or LOW	5.0	2.0	3.0	3.0	ns

Note 5: Voltage range 5.0 is 5.0V ± 0.5V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	20	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



24 Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1988
Revised December 1998

74ACT823
9-Bit D-Type Flip-Flop

General Description

The ACT823 is a 9-bit buffered register. It features Clock Enable and Clear which are ideal for parity bus interfacing in high performance microprogramming systems. The ACT823 offers noninverting outputs and is fully compatible with AMD's Am29823.

Features

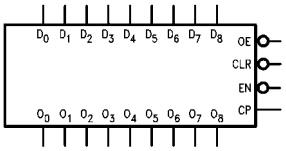
- Outputs source/sink 24 mA
- 3-STATE outputs for bus interfacing
- Inputs and outputs are on opposite sides
- ACT823 has TTL-compatible inputs

Ordering Code:

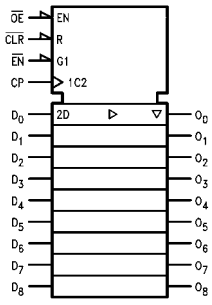
Order Number	Package Number	Package Description
74ACT823SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT823MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT823SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. (SPC not available in Tape and Reel.)

Logic Symbols

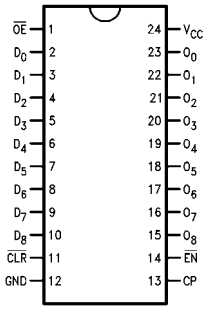


IEEE/IEC



Connection Diagram

Pin Assignment for DIP, SOIC and TSSOP



Pin Descriptions

Pin Names	Description
D_0–D_8	Data Inputs
O_0–O_8	Data Outputs
$\overline{OE}$	Output Enable
$\overline{CLR}$	Clear
CP	Clock Input
$\overline{EN}$	Clock Enable

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Functional Description

The ACT823 consists of nine D-type edge-triggered flip-flops. These have 3-STATE outputs for bus systems organized with inputs and outputs on opposite sides. The buffered clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops. In addition to the Clock and Output Enable pins, there are Clear ($\overline{CLR}$) and Clock Enable ($\overline{EN}$) pins. These devices are ideal for parity bus interfacing in high performance systems.

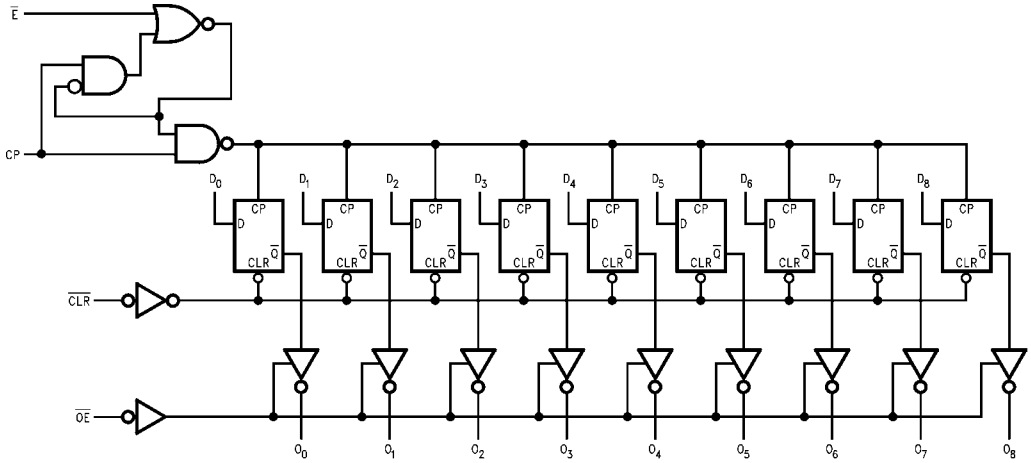
When $\overline{CLR}$ is LOW and $\overline{OE}$ is LOW, the outputs are LOW. When $\overline{CLR}$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}$ is HIGH, the outputs do not change state, regardless of the data or clock input transitions.

Function Table

Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	D	Q	O	
H	X	L	⌐	L	L	Z	High Z
H	X	L	⌐	H	H	Z	High Z
H	L	X	X	X	L	Z	Clear
L	L	X	X	X	L	L	Clear
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	H	L	⌐	L	L	Z	Load
H	H	L	⌐	H	H	Z	Load
L	H	L	⌐	L	L	L	Load
L	H	L	⌐	H	H	H	Load

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to 7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		4.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
			5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
				4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	µA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ −2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80	µA	$V_{IN} = V_{CC}$ or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ $C_L = 50pF$			$T_A = -40°C$ to $+85°C$ $C_L = 50$ pF		Units
		(Note 4)	Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	5.0	120	158		109		MHz
t_{PLH}	Propagation Delay CP to O_n	5.0	1.5	5.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay CP to O_n	5.0	2.0	5.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	8.0	13.5	2.0	15.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	1.5	6.0	10.5	1.5	11.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.0	6.5	11.0	1.5	12.0	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	6.5	11.0	1.5	12.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	6.0	10.5	1.5	11.5	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

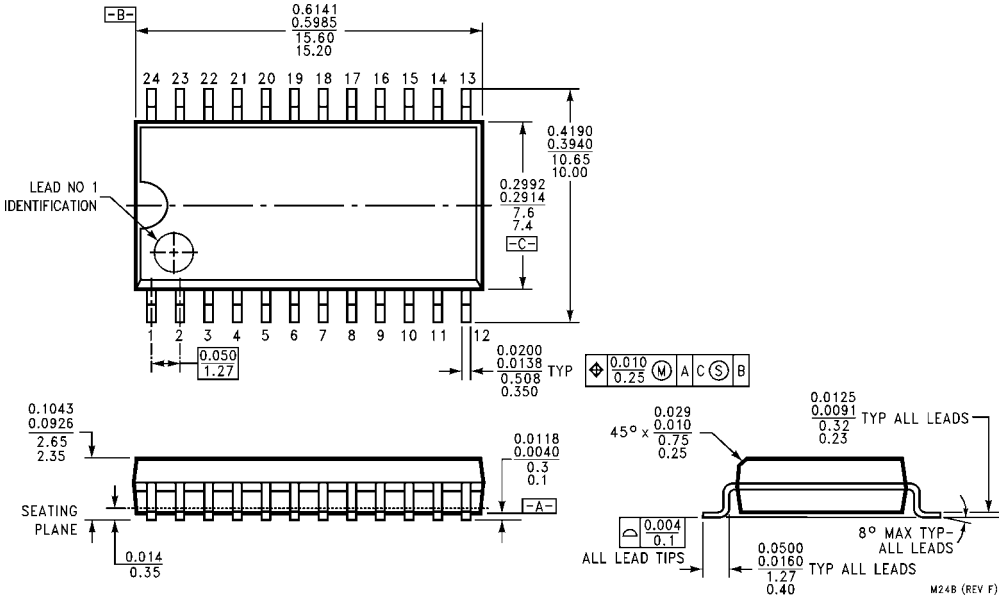
Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$ $C_L = 50$ pF	Units
		(Note 5)	Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D to CP	5.0	0.5	2.5	2.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	2.5	2.5	ns
t_S	Setup Time, HIGH or LOW $\overline{EN}$ to CP	5.0	0	2.0	2.5	ns
t_H	Hold Time, HIGH or LOW $\overline{EN}$ to CP	5.0	0	1.0	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.5	4.5	5.5	ns
t_W	$\overline{CLR}$ Pulse Width, LOW	5.0	3.0	5.5	5.5	ns
t_{rec}	$\overline{CLR}$ to CP Recovery Time	5.0	1.5	3.5	4.0	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

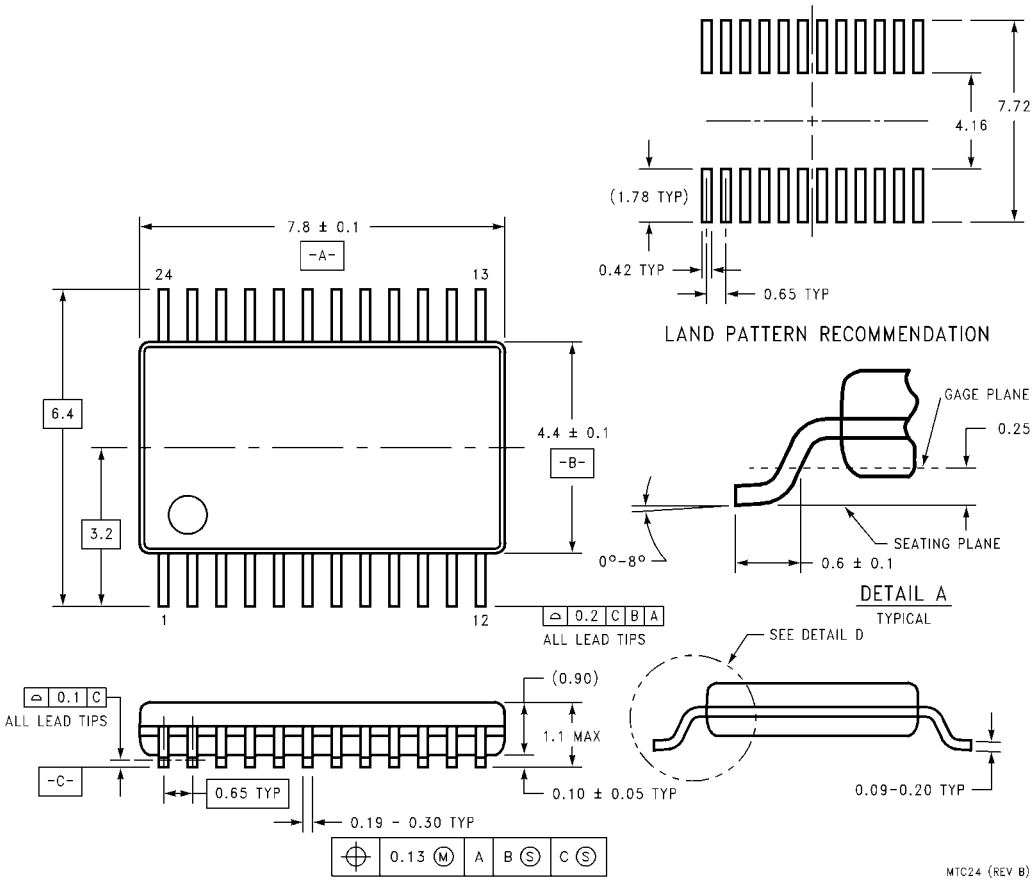
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	44	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



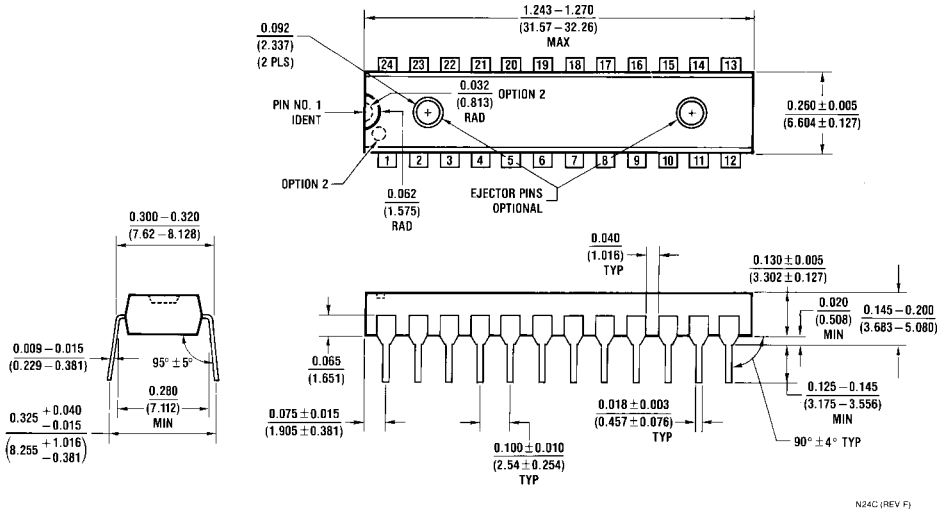
24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1988
Revised November 1998

74ACT825
8-Bit D-Type Flip-Flop

General Description

The ACT825 is an 8-bit buffered register. They have Clock Enable and Clear features which are ideal for parity bus interfacing in high performance microprogramming systems. Also included are multiple enables that allow multiuse control of the interface. The ACT825 has noninverting outputs and is fully compatible with AMD's Am29825.

Features

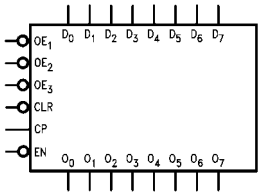
- Outputs source/sink 24 mA
- Inputs and outputs are on opposite sides
- ACT825 has TTL-compatible inputs

Ordering Code:

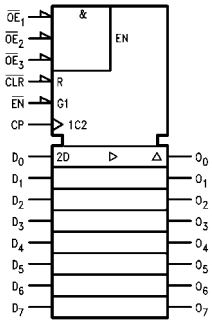
Order Number	Package Number	Package Description
74ACT825SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT825MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT825SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols

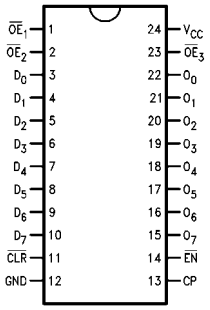


IEEE/IEC



Connection Diagram

Pin Assignment for DIP, SOIC and TSSOP



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
O_0–O_7	Data Outputs
$\overline{OE}_1$, $\overline{OE}_2$, $\overline{OE}_3$	Output Enables
$\overline{EN}$	Clock Enable
$\overline{CLR}$	Clear
CP	Clock Input

FACT™ is a trademark of Fairchild Semiconductor.

Functional Description

The ACT825 consists of eight D-type edge-triggered flip-flops. These devices have 3-STATE outputs for bus systems, organized in a broadside pinning. In addition to the clock and output enable pins, the buffered clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}_1$, $\overline{OE}_2$ and $\overline{OE}_3$ LOW, the contents of the flip-flops are available at the outputs. When one of $\overline{OE}_1$, $\overline{OE}_2$ or $\overline{OE}_3$ is HIGH, the outputs go to the high impedance state.

Operation of the $\overline{OE}$ input does not affect the state of the flip-flops. The ACT825 has Clear ($\overline{CLR}$) and Clock Enable ($\overline{EN}$) pins. These pins are ideal for parity bus interfacing in high performance systems.

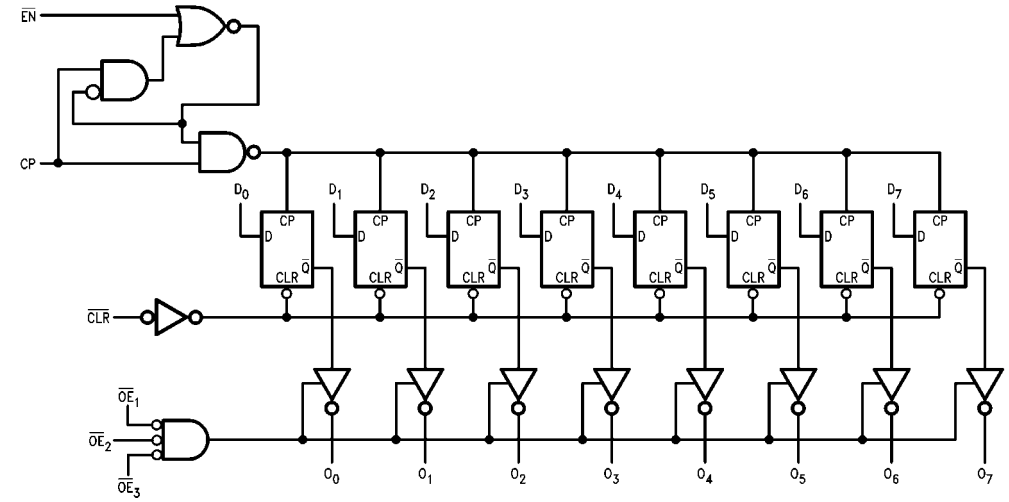
When $\overline{CLR}$ is LOW and $\overline{OE}$ is LOW, the outputs are LOW. When $\overline{CLR}$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When $\overline{EN}$ is HIGH, the outputs do not change state, regardless of the data or clock input transitions.

Function Table

Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	D_n	Q	O	
H	X	L	⌐	L	L	Z	High-Z
H	X	L	⌐	H	H	Z	High-Z
H	L	X	X	X	L	Z	Clear
L	L	X	X	X	L	L	Clear
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	H	L	⌐	L	L	Z	Load
H	H	L	⌐	H	H	Z	Load
L	H	L	⌐	L	L	L	Load
L	H	L	⌐	H	H	H	Load

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to 7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	+0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8		V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	5.0	120	158		109		MHz
t_{PLH}	Propagation Delay CP to O_n	5.0	1.5	5.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay CP to O_n	5.0	2.0	5.5	9.5	1.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	8.0	13.5	2.0	15.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	1.5	6.0	10.5	1.5	11.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.0	6.5	11.0	1.5	12.0	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	6.5	11.0	1.5	12.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	6.0	10.5	1.5	11.5	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

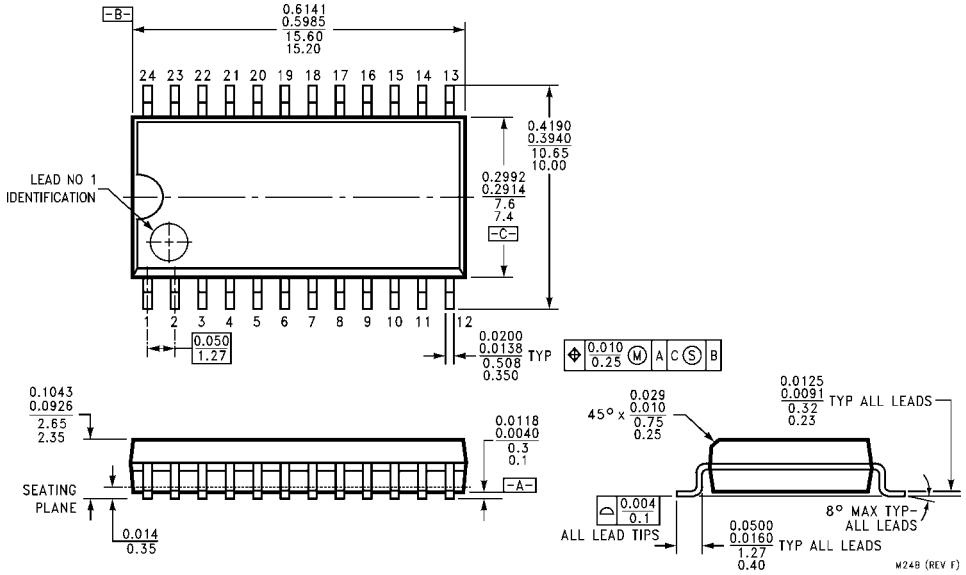
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	0.5	2.5	2.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	2.5	2.5	ns
t_S	Setup Time, HIGH or LOW $\overline{EN}$ to CP	5.0	0	2.0	2.5	ns
t_H	Hold Time, HIGH or LOW $\overline{EN}$ to CP	5.0	0	1.0	1.0	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.5	4.5	5.5	ns
t_W	$\overline{CLR}$ Pulse Width, LOW	5.0	3.0	5.5	5.5	ns
t_{rec}	$\overline{CLR}$ to CP Recovery Time	5.0	1.5	3.5	4.0	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

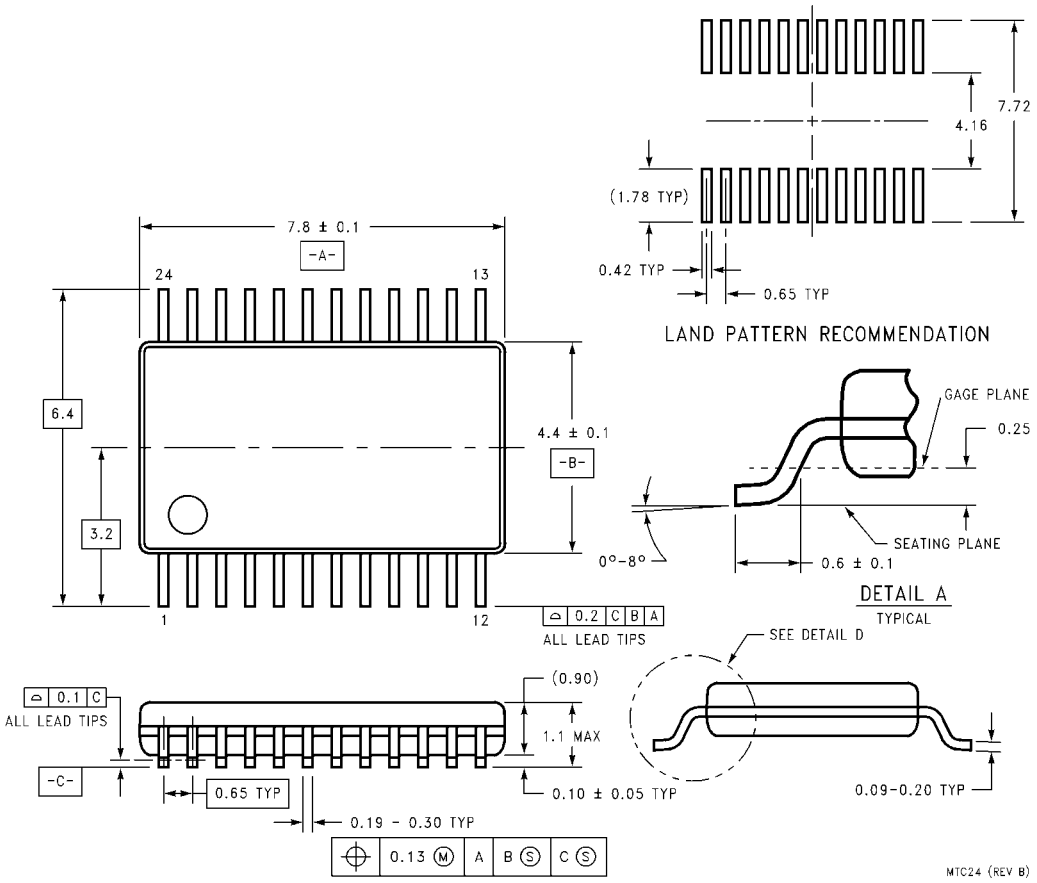
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	44	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



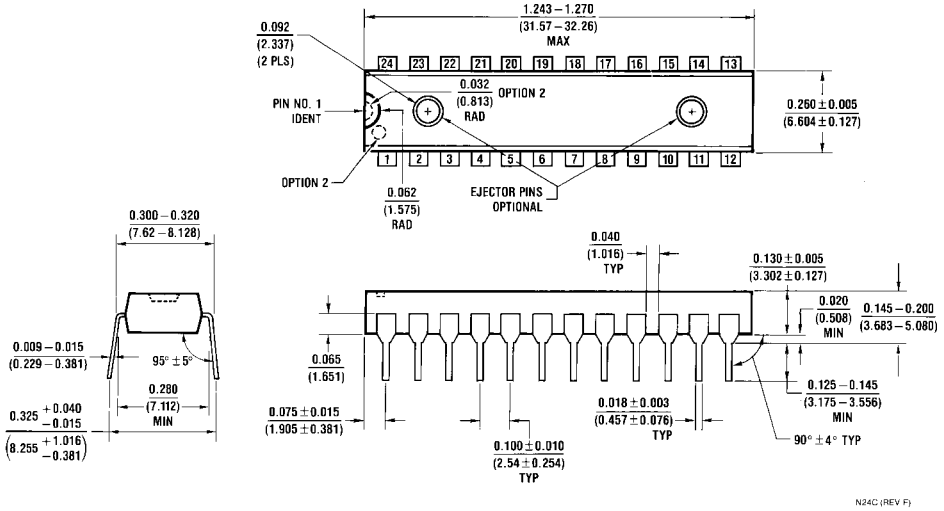
24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

November 1988
Revised November 1998

74ACT841
10-Bit Transparent Latch with 3-STATE Outputs

General Description

The ACT841 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths or buses carrying parity. The ACT841 is a 10-bit transparent latch, a 10-bit version of the ACT373.

Features

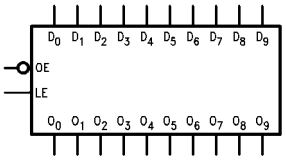
- ACT841 has TTL-compatible inputs
- Outputs source/sink 24 mA
- Non-inverting 3-STATE outputs

Ordering Code:

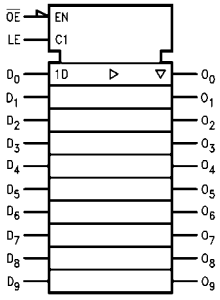
Order Number	Package Number	Package Description
74ACT841SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT841MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACT841SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. (SPC not available in Tape and Reel.)

Logic Symbols

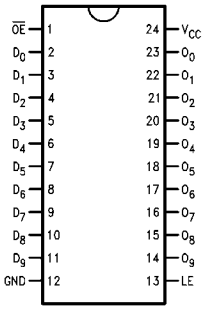


IEEE/IEC



Connection Diagram

Pin Assignment for DIP, SOIC and TSSOP



Pin Descriptions

Pin Names	Description
D_0–D_9	Data Inputs
O_0–O_9	3-STATE Outputs
$\overline{OE}$	Output Enable
LE	Latch Enable

FACT™ is a trademark of Fairchild Semiconductor Corporation.

Functional Description

The ACT841 consists of ten D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition.

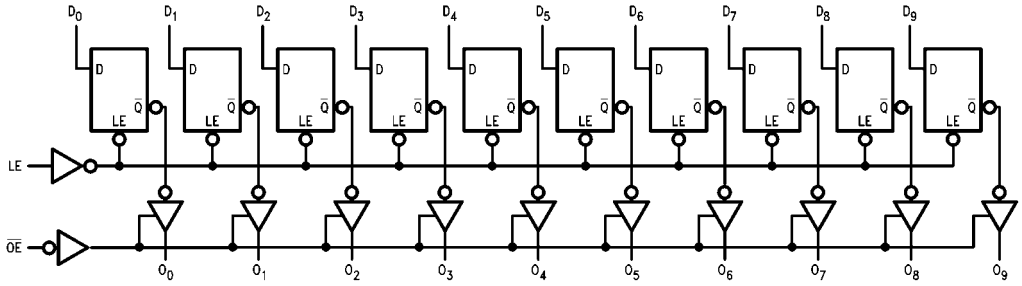
On the LE HIGH-to-LOW transition, the data that meets the setup and hold time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

Function Table

Inputs			Internal	Output	Function
$\overline{OE}$	LE	D	Q	O	
X	X	X	X	Z	High Z
H	H	L	L	Z	High Z
H	H	H	H	Z	High Z
H	L	X	NC	Z	Latched
L	H	L	L	L	Transparent
L	H	H	H	H	Transparent
L	L	X	NC	NC	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	μA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to O_n	5.0	2.0	5.5	9.5	2.0	10.0	ns
t_{PHL}	Propagation Delay D_n to O_n	5.0	2.0	5.5	9.5	2.0	10.0	ns
t_{PLH}	Propagation Delay LE to O_n	5.0	2.0	5.5	9.0	2.0	10.0	ns
t_{PHL}	Propagation Delay LE to O_n	5.0	2.0	5.5	9.0	2.0	10.0	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.0	5.5	9.5	2.0	10.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.0	5.5	9.5	2.0	10.5	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	2.0	6.0	10.5	2.0	11.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	2.0	6.0	10.5	2.0	11.0	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

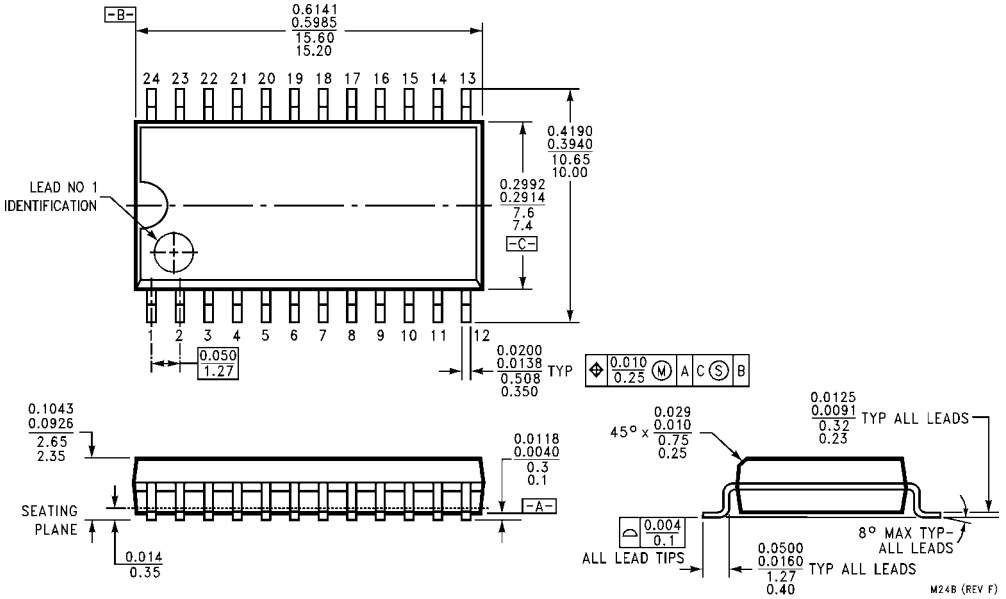
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	–0.5	0.5	1.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0.5	2.0	2.0	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	3.5	3.5	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

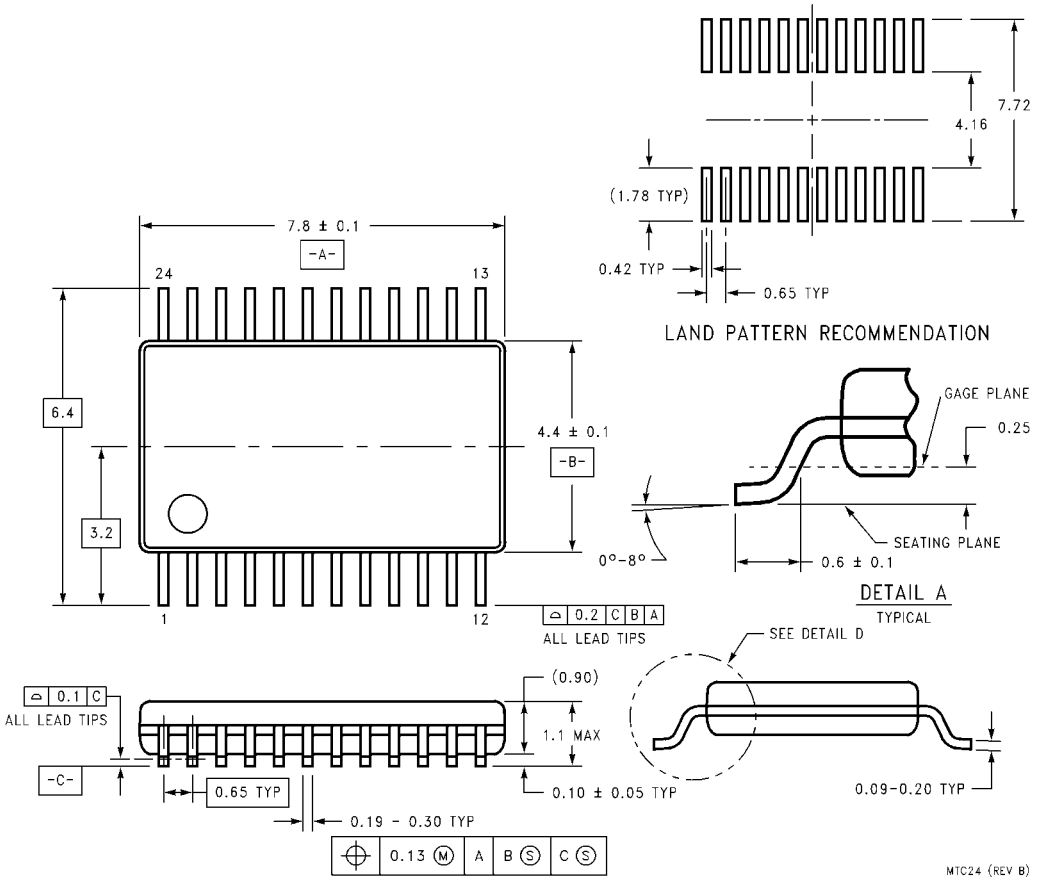
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	44	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



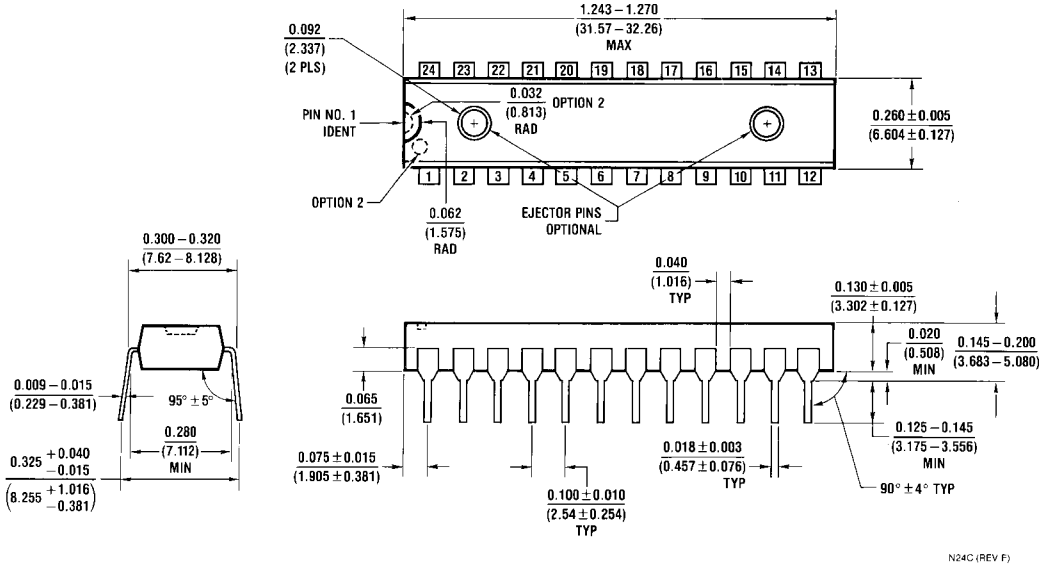
24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1988
Revised December 1998

74ACT843
9-Bit Transparent Latch

General Description

The ACT843 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths.

The ACT843 is functionally and pin compatible with AMD's Am29843.

Features

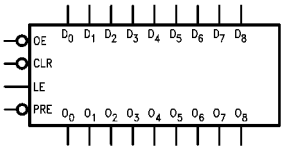
- Has TTL-compatible inputs
- 3-STATE outputs for bus interfacing

Ordering Code:

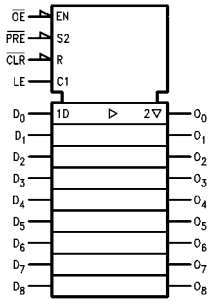
Order Number	Package Number	Package Description
74ACT843SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACT843SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. (SPC not available in Tape and Reel.)

Logic Symbols

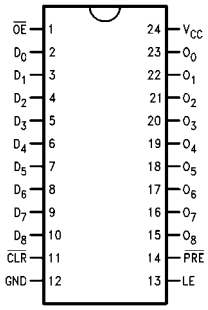


IEEE/IEC



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
D_0–D_8	Data Inputs
O_0–O_8	Data Outputs
$\overline{OE}$	Output Enable
LE	Latch Enable
$\overline{CLR}$	Clear
$\overline{PRE}$	Preset

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Functional Description

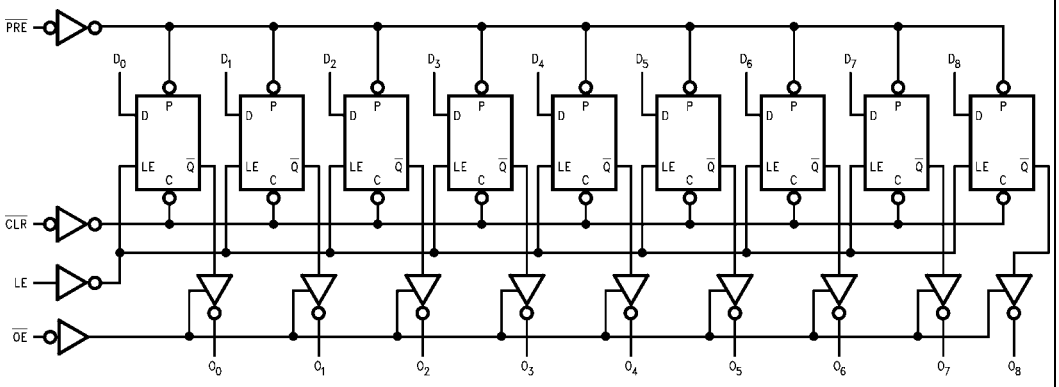
The ACT843 consists of nine D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition. On the LE HIGH-to-LOW transition, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state. In addition to the LE and $\overline{OE}$ pins, the ACT843 has a Clear ($\overline{CLR}$) pin and a Preset ($\overline{PRE}$) pin. These pins are ideal for parity bus interfacing in high performance systems. When $\overline{CLR}$ is LOW, the outputs are LOW if $\overline{OE}$ is LOW. When $\overline{CLR}$ is HIGH, data can be entered into the latch. When $\overline{PRE}$ is LOW, the outputs are HIGH if $\overline{OE}$ is LOW. Preset overrides $\overline{CLR}$.

Function Tables

Inputs					Internal	Outputs	Function
$\overline{CLR}$	$\overline{PRE}$	$\overline{OE}$	LE	D	Q	O	
H	H	H	H	L	L	Z	High Z
H	H	H	H	H	H	Z	High Z
H	H	H	L	X	NC	Z	Latched
H	H	L	H	L	L	L	Transparent
H	H	L	H	H	H	H	Transparent
H	H	L	L	X	NC	NC	Latched
H	L	L	X	X	H	H	Preset
L	H	L	X	X	L	L	Clear
L	L	L	X	X	H	H	Preset
L	H	H	L	X	L	Z	Clear/High Z
H	L	H	L	X	H	Z	Preset/High Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} +0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_O = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 4)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to O_n	5.0	2.5	5.5	9.5	2.0	10.0	ns
t_{PHL}	Propagation Delay D_n to O_n	5.0	2.5	5.5	9.5	2.0	10.0	ns
t_{PLH}	Propagation Delay LE to O_n	5.0	2.5	5.5	9.0	2.0	10.0	ns
t_{PHL}	Propagation Delay LE to O_n	5.0	2.5	5.5	9.0	2.0	10.0	ns
t_{PLH}	Propagation Delay $\overline{PRE}$ to O_n	5.0	2.5	6.5	14.0	2.0	16.0	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	7.5	15.5	2.0	17.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	2.5	6.0	10.5	2.0	11.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	2.5	6.0	10.5	2.0	11.0	ns
t_{PHL}	Propagation Delay $\overline{PRE}$ to O_n	5.0	2.5	6.0	10.5	2.0	11.0	ns
t_{PLH}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	5.5	9.5	2.0	10.5	ns

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

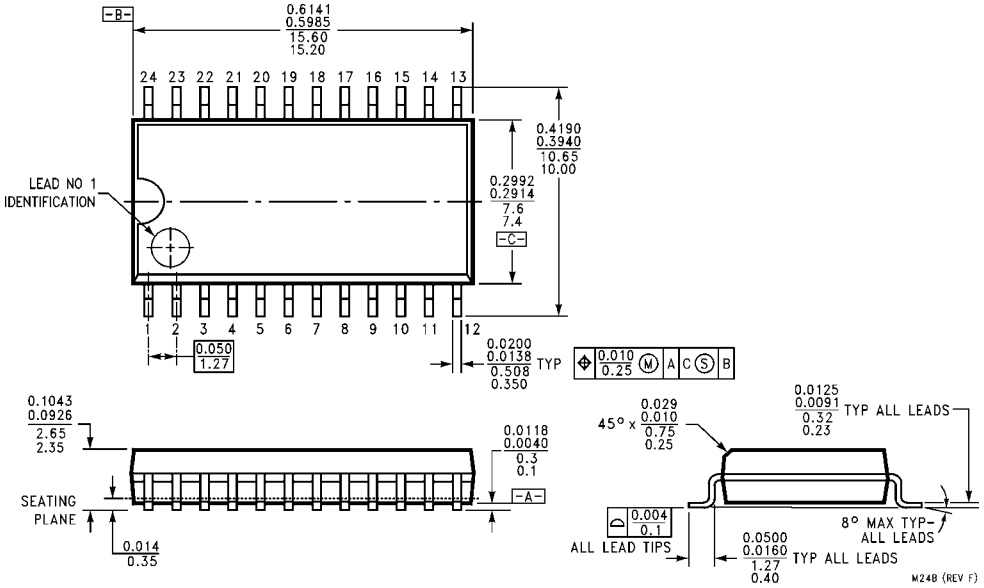
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	−0.5	0.5	1.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0.5	2.0	2.0	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	3.5	3.5	ns
t_W	$\overline{PRE}$ Pulse Width, LOW	5.0	5.0	8.5	10.0	ns
t_W	$\overline{CLR}$ Pulse Width, LOW	5.0	5.5	9.5	11.0	ns
t_{rec}	$\overline{PRE}$ Recovery Time	5.0	0.5	2.0	2.0	ns
t_{rec}	$\overline{CLR}$ Recovery Time	5.0	−0.5	1.0	1.0	ns

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

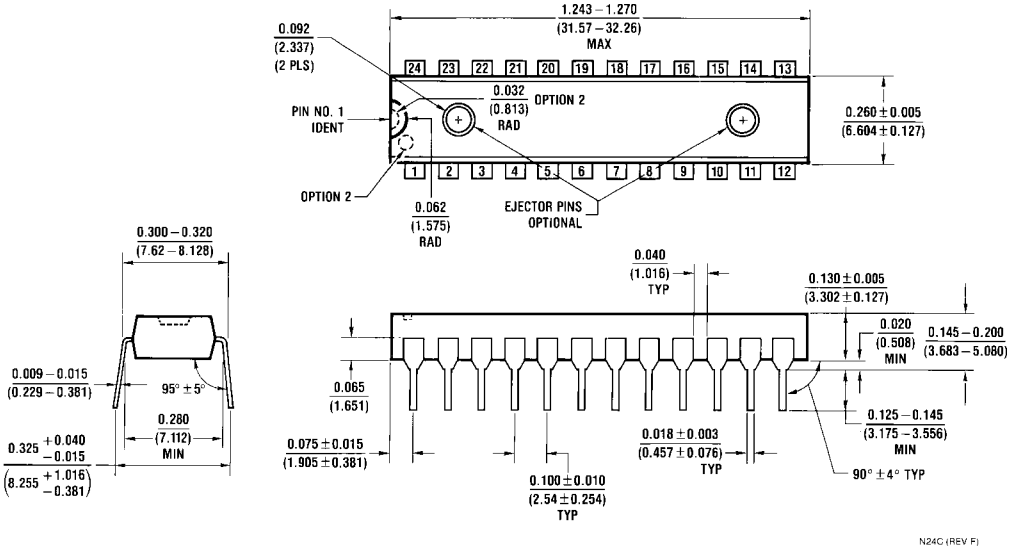
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	44	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1990
Revised December 1998

74ACT899
9-Bit Latchable Transceiver with Parity Generator/Checker

General Description

The ACT899 is a 9-bit to 9-bit parity transceiver with transparent latches. The device can operate as a feed-through transceiver or it can generate/check parity from the 8-bit data busses in either direction. The ACT899 features independent latch enables for the A-to-B direction and the B-to-A direction, a select pin for ODD/$\overline{\text{EVEN}}$ parity, and separate error signal output pins for checking parity.

Features

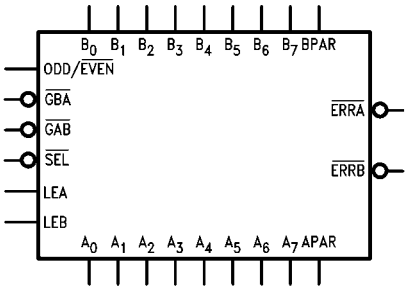
- Latchable transceiver with output sink of 24 mA
- Option to select generate parity and check or "feed-through" data/parity in directions A-to-B or B-to-A
- Independent latch enable for A-to-B and B-to-A directions
- Select pin for ODD/$\overline{\text{EVEN}}$ parity
- $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ output pins for parity checking
- Ability to simultaneously generate and check parity
- May be used in system applications in place of the 280
- May be used in system applications in place of the 657 and 373 (no need to change T/$\overline{\text{R}}$ to check parity)

Ordering Code:

Order Number	Package Number	Package Description
74ACT899QC	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450" Square

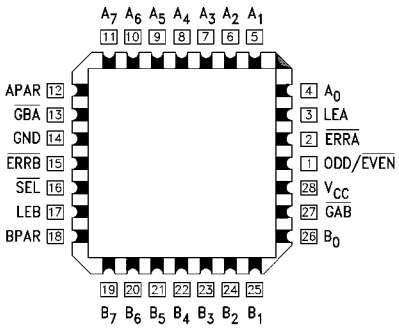
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram

Pin Assignment for PCC



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Pin Descriptions

Pin Names	Description
A_0–A_7	A Bus Data Inputs/Data Outputs
B_0–B_7	B Bus Data Inputs/Data Outputs
APAR, BPAR	A and B Bus Parity Inputs
ODD/$\overline{\text{EVEN}}$	ODD/$\overline{\text{EVEN}}$ Parity Select, Active LOW for EVEN Parity
$\overline{\text{GBA}}$, $\overline{\text{GAB}}$	Output Enables for A or B Bus, Active LOW
$\overline{\text{SEL}}$	Select Pin for Feed-Through or Generate Mode, LOW for Generate Mode
LEA, LEB	Latch Enables for A and B Latches, HIGH for Transparent Mode
$\overline{\text{ERRA}}$, $\overline{\text{ERRB}}$	Error Signals for Checking Generated Parity with Parity In, LOW if Error Occurs

Functional Description

The ACT899 has three principal modes of operation which are outlined below. These modes apply to both the A-to-B and B-to-A directions.

- Bus A (B) communicates to Bus B (A), parity is generated and passed on to the B (A) Bus as BPAR (APAR). If LEB (LEA) is HIGH and the Mode Select ($\overline{\text{SEL}}$) is LOW, the parity generated from B[0:7] (A[0:7]) can be checked and monitored by $\overline{\text{ERRB}}$ ($\overline{\text{ERRA}}$).
- Bus A (B) communicates to Bus B (A) in a feed-through mode if $\overline{\text{SEL}}$ is HIGH. Parity is still generated and checked as $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ in the feed-through mode (can be used as an interrupt to signal a data/parity bit error to the CPU).
- Independent Latch Enables (LEA and LEB) allow other permutations of generating/checking (see Function Table).

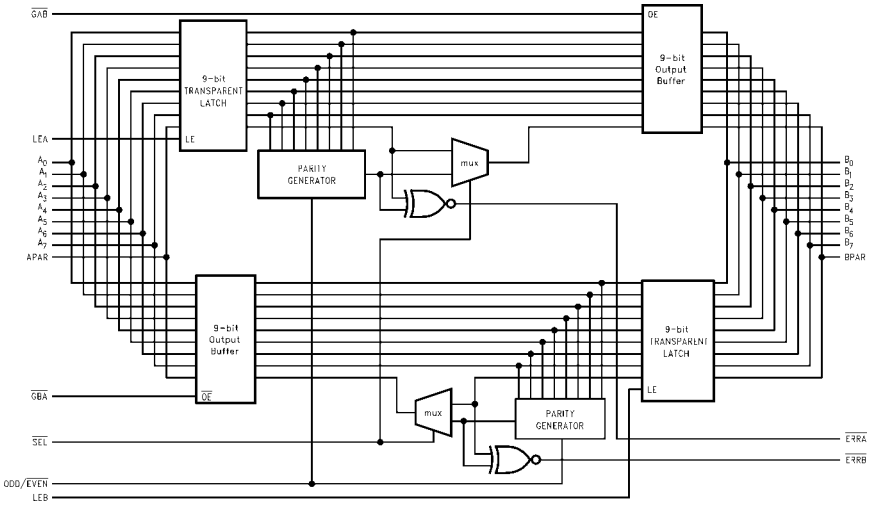
Function Table

Inputs					Operation
$\overline{\text{GAB}}$	$\overline{\text{GBA}}$	$\overline{\text{SEL}}$	LEA	LEB	
H	H	X	X	X	Busses A and B are 3-STATE.
H	L	L	L	H	Generates parity from B[0:7] based on O/$\overline{\text{E}}$ (Note 1). Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$.
H	L	L	H	H	Generates parity from B[0:7] based on O/$\overline{\text{E}}$. Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$. Generated parity also fed back through the A latch for generate/check as $\overline{\text{ERRA}}$.
H	L	L	X	L	Generates parity from B latch data based on O/$\overline{\text{E}}$. Generated parity → APAR. Generated parity checked against latched BPAR and output as $\overline{\text{ERRB}}$.
H	L	H	X	H	BPAR/B[0:7] → APAR/A0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$.
H	L	H	H	H	BPAR/B[0:7] → APAR/A[0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{\text{ERRB}}$. Generated parity also fed back through the A latch for generate/check as $\overline{\text{ERRA}}$.
L	H	L	H	L	Generates parity for A[0:7] based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$.
L	H	L	H	H	Generates parity from A[0:7] based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$. Generated parity also fed back through the B latch for generate/check as $\overline{\text{ERRB}}$.
L	H	L	L	X	Generates parity from A latch data based on O/$\overline{\text{E}}$. Generated parity → BPAR. Generated parity checked against latched APAR and output as $\overline{\text{ERRA}}$.
L	H	H	H	L	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$.
L	H	H	H	H	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{\text{ERRA}}$. Generated parity also fed back through the B latch for generate/check as $\overline{\text{ERRB}}$.

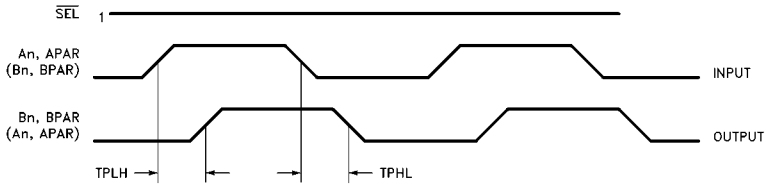
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Note 1: O/$\overline{\text{E}}$ = ODD/$\overline{\text{EVEN}}$

Functional Block Diagram



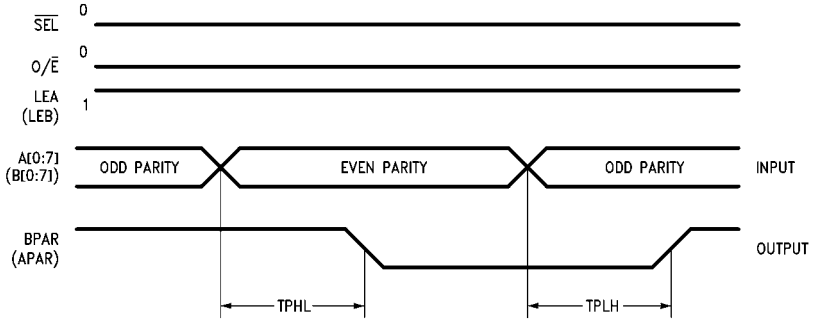
AC Path



A_n, APAR → B_n, BPAR

(B_n, BPAR → A_n, APAR)

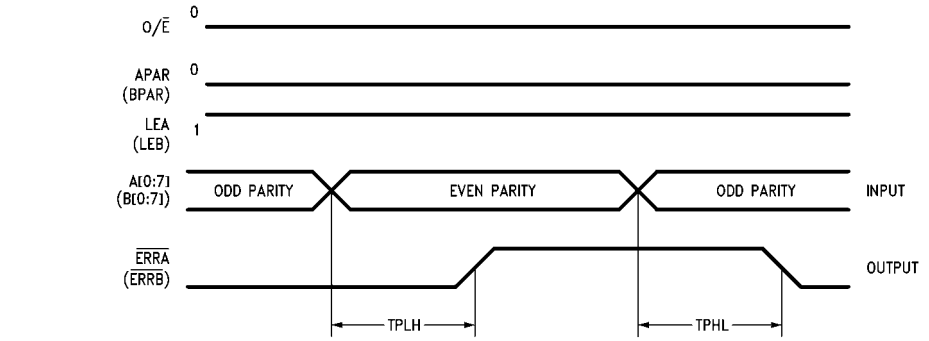
FIGURE 1.



A_n → BPAR

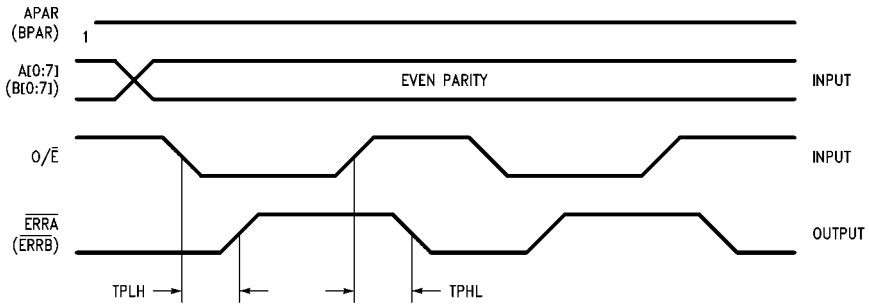
(B_n → APAR)

FIGURE 2.



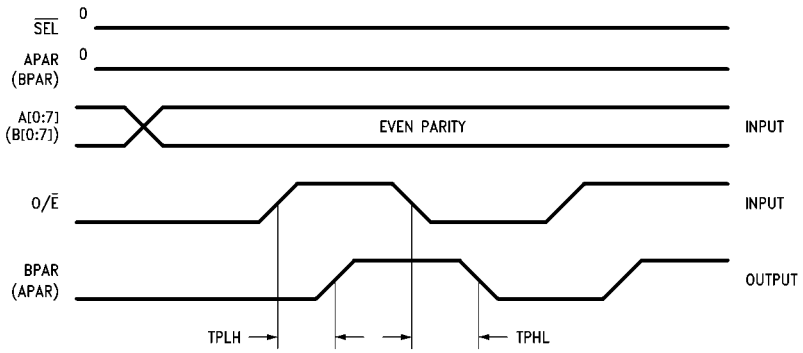
$A_n \rightarrow \overline{ERRA}$
($B_n \rightarrow \overline{ERRB}$)

FIGURE 3.



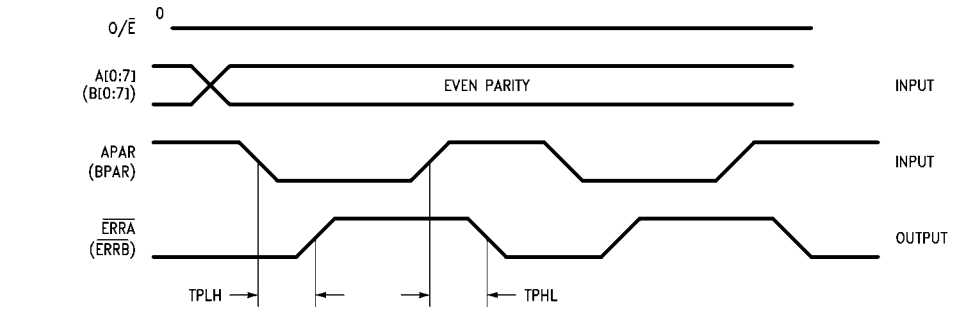
O/$\overline{E} \rightarrow \overline{ERRA}$
O/$\overline{E} \rightarrow \overline{ERRB}$

FIGURE 4.



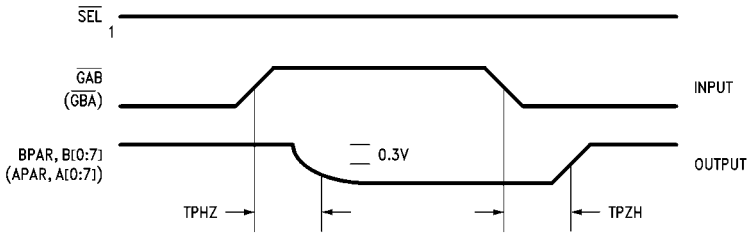
O/$\overline{E} \rightarrow$ BPAR
(O/$\overline{E} \rightarrow$ APAR)

FIGURE 5.



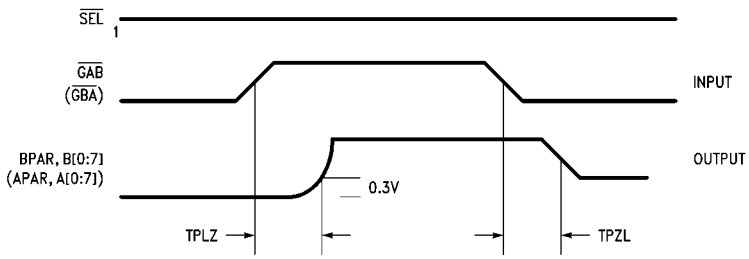
APAR → $\overline{\text{ERRA}}$
(BPAR → $\overline{\text{ERRB}}$)

FIGURE 6.



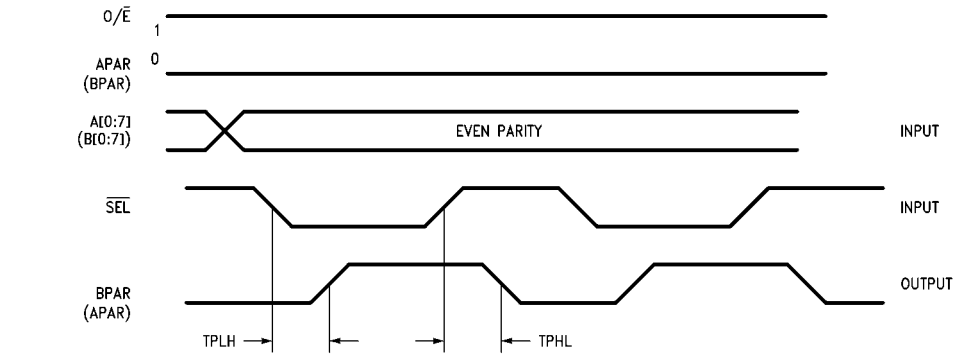
ZH, HZ

FIGURE 7.



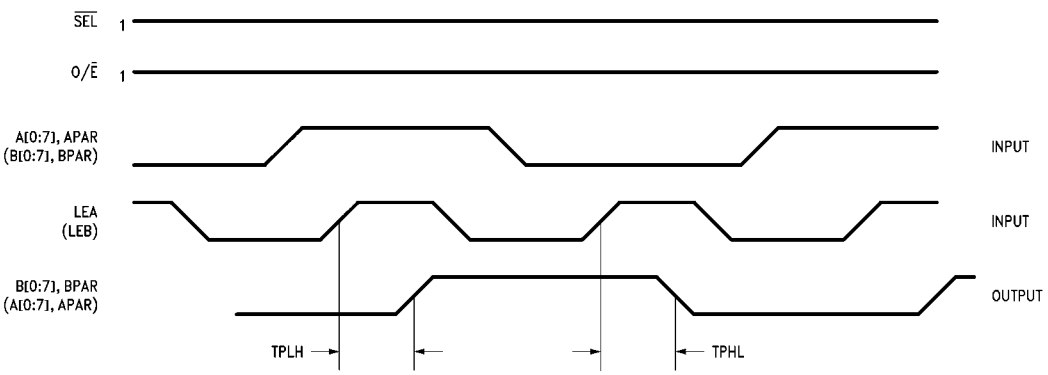
ZL, LZ

FIGURE 8.



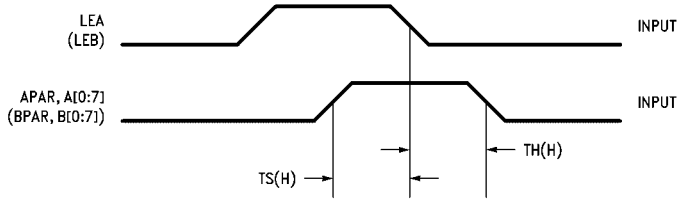
$\overline{\text{SEL}}$ → BPAR
($\overline{\text{SEL}}$ → APAR)

FIGURE 9.



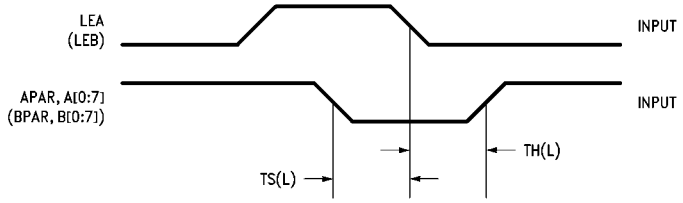
LEA → BPAR, B[0:7]
(LEB → APAR, A[0:7])

FIGURE 10.



TS(H), TH(H)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 11.



TS(L), TH(L)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 12.

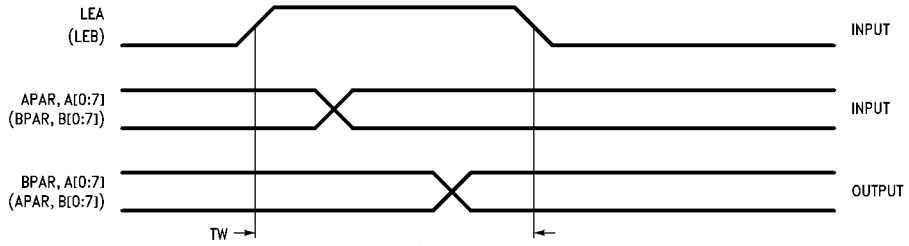


FIGURE 13.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA
Junction Temperature (T_J)	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{IN}	Maximum Input	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
	Leakage Current						
I_{OZ}	Maximum 3-STATE	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent	5.5		8.0	80.0	μA	V_{IN} = V_{CC}
	Supply Current						or GND

Note 3: Maximum of 9 outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units	Fig. No.
			Min	Typ	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to B_n, A_n	5.0	2.5	7.5	11.5	2.5	12.0	ns	Figure 1
t_{PLH} t_{PHL}	Propagation Delay APAR, BPAR to BPAR, APAR	5.0	1.5	6.0	8.5	1.5	9.0	ns	Figure 1
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to BPAR, APAR	5.0	2.5	8.5	12.0	2.5	12.5	ns	Figure 2
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$	5.0	2.0	8.0	11.5	2.0	12.0	ns	Figure 3
t_{PLH} t_{PHL}	Propagation Delay ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$	5.0	2.0	8.0	11.5	2.0	12.0	ns	Figure 4
t_{PLH} t_{PHL}	Propagation Delay ODD/$\overline{EVEN}$ to APAR, BPAR	5.0	2.5	8.0	11.5	2.5	12.0	ns	Figure 5
t_{PLH} t_{PHL}	Propagation Delay APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$	5.0	1.5	7.5	10.5	1.5	11.5	ns	Figure 6
t_{PLH} t_{PHL}	Propagation Delay $\overline{SEL}$ to APAR, BPAR	5.0	1.5	6.5	9.0	1.5	9.5	ns	Figure 9
t_{PLH} t_{PHL}	Propagation Delay LEB to A_n, B_n	5.0	2.5	7.0	10.5	2.5	11.0	ns	Figure 10 Figure 11
t_{PLH} t_{PHL}	Propagation Delay LEA to APAR, BPAR	5.0	2.0	8.0	11.5	2.0	12.0	ns	Figure 10 Figure 11
t_{PLH} t_{PHL}	Propagation Delay LEA, LEB to $\overline{ERRA}$, $\overline{ERRB}$	5.0	2.5	8.0	11.5	2.5	12.0	ns	Figure 12
t_{PZH} t_{PZL}	Output Enable Time $\overline{GBA}$ or $\overline{GAB}$ to A_n, B_n	5.0	2.5	7.0	10.5	2.5	11.0	ns	Figure 7 Figure 8
t_{PZH} t_{PZL}	Output Enable Time $\overline{GBA}$ or $\overline{GAB}$ to BPAR or APAR	5.0	1.5	6.0	9.0	1.5	9.5	ns	Figure 7 Figure 8
t_{PHZ} t_{PHL}	Output Disable Time $\overline{GBA}$ or $\overline{GAB}$ to A_n, B_n	5.0	1.5	6.5	9.5	1.5	9.5	ns	Figure 7 Figure 8
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{GBA}$ or $\overline{GAB}$ to BPAR, APAR	5.0	1.5	6.5	9.5	1.5	9.5	ns	Figure 7 Figure 8

Note 5: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

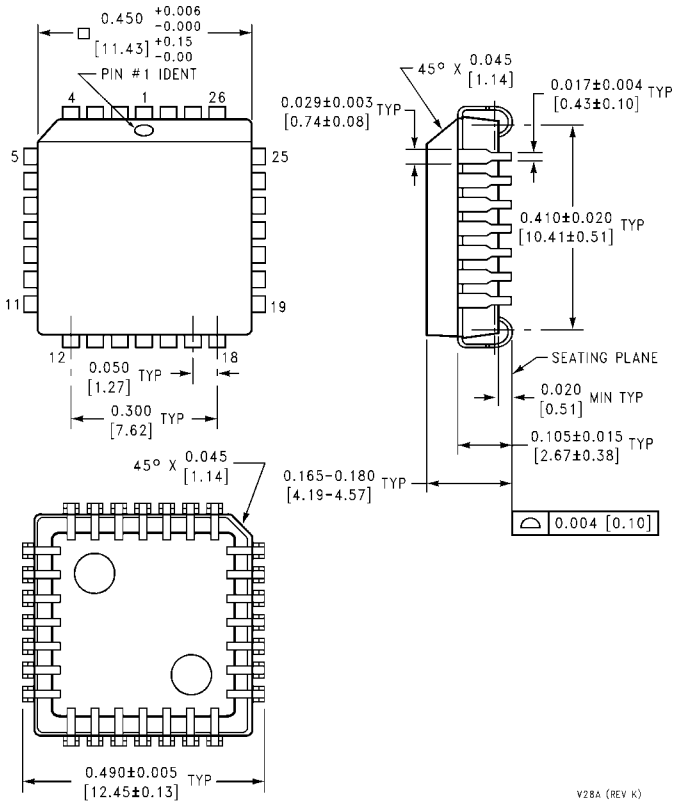
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units	Fig. No.
			Guaranteed Minimum			
t_S	Setup Time, HIGH or LOW A_n, B_n, PAR to LEA, LEB	5.0	3.0	3.0	ns	Figure 11 Figure 12
t_H	Hold Time, HIGH or LOW A_n, B_n, PAR to LEA, LEB	5.0	1.5	1.5	ns	Figure 11 Figure 12
t_W	Pulse Width for LEB, LEA	5.0	4.0	4.0	ns	Figure 13

Note 6: Voltage Range 5.0 = 5.0V ± 0.5V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	210	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted



28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450" Square
Package Number V28A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1990
Revised April 1999

74ACTQ00
Quiet Series™ Quad 2-Input NAND Gate

General Description

The ACTQ00 contains four 2-input NAND gates and utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

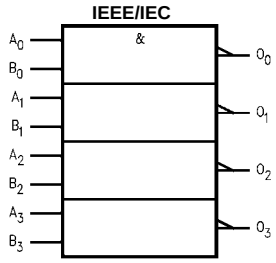
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- Has TTL-compatible inputs

Ordering Code:

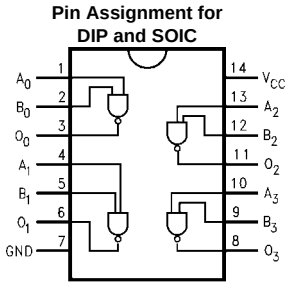
Order Number	Package Number	Package Description
74ACTQ00SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACTQ00PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

FACT™, Quiet Series™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source	
or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	125 mV/ns
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76	V	I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44	V	I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n−1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	2.0		7.5	2.0	8.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	2.0		7.5	2.0	8.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ±0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	74	pF	V_{CC} = 5.0V

FACT™ Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

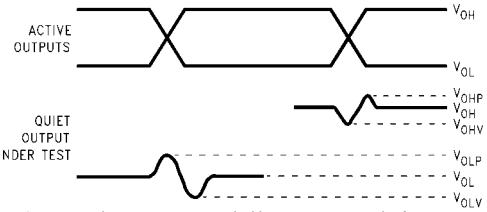
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the word generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope



Note 9: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 10: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level.V_{IH} until the output begins to oscillate or steps out a mine of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

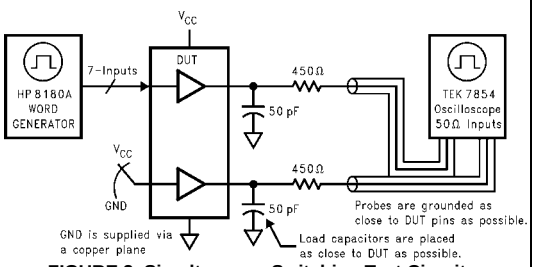
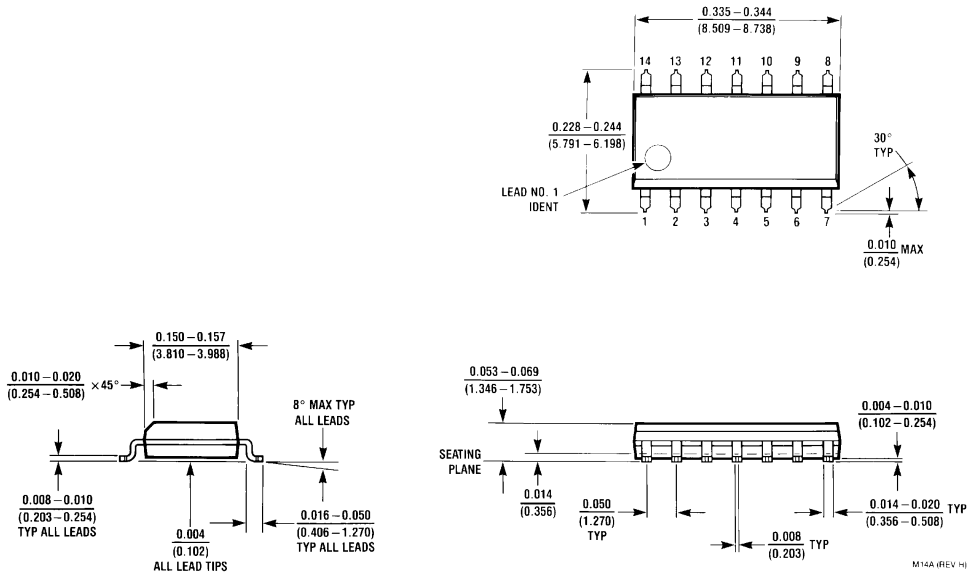


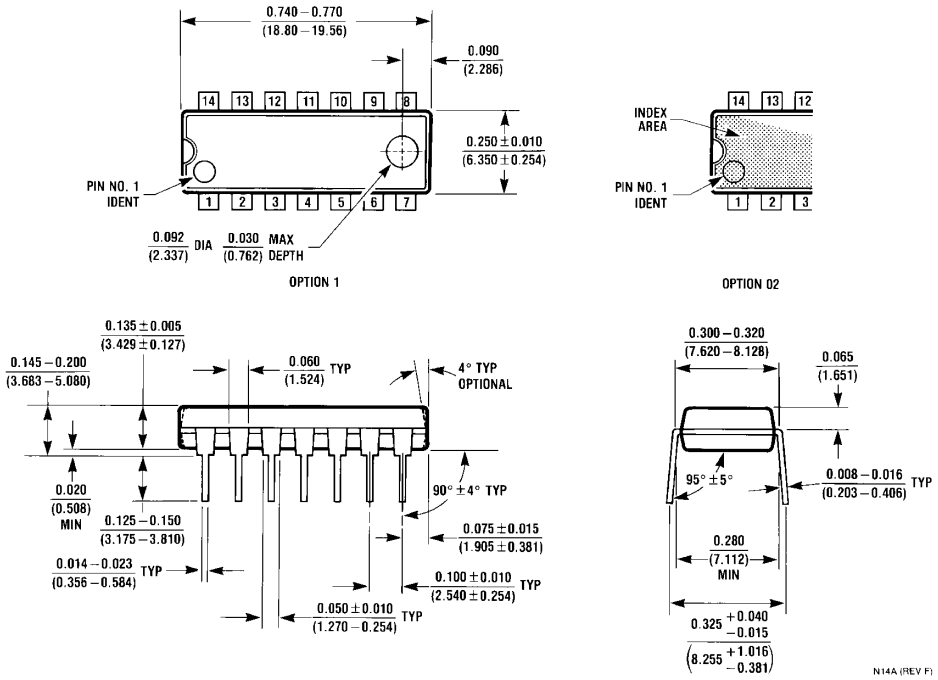
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP) JEDEC MS-001, 0.300" Wide
Package Number N14A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

August 1990
Revised November 1999

74ACTQ02
Quad 2-Input NOR Gate

General Description

The ACTQ02 contains four, 2-input NOR gates.

The ACTQ utilize Fairchild's Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

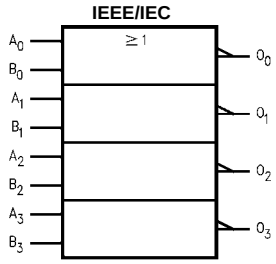
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- ACTQ02 has TTL-compatible inputs

Ordering Code:

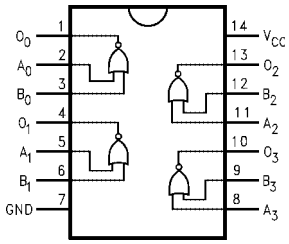
Order Number	Package Number	Package Description
74ACTQ02SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACTQ02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ02PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

FACT™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	1.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output |Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Plastic DIP package

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n−1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	2.0	5.0	7.5	2.0	8.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	2.0	5.0	7.5	2.0	8.0	ns
t_{OSHL}, t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	75	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.

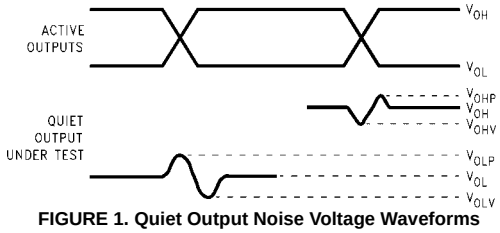


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 9: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 10: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

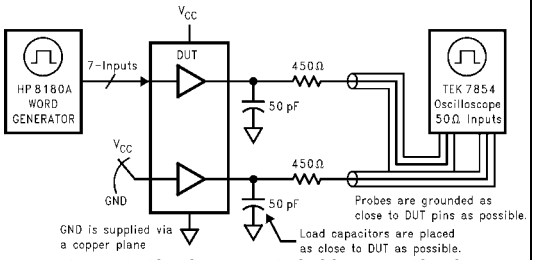
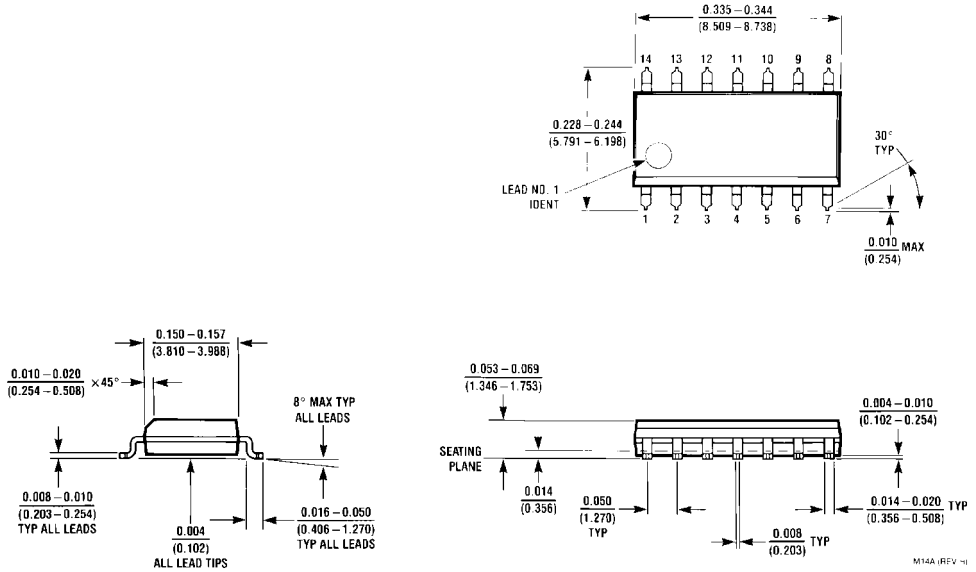


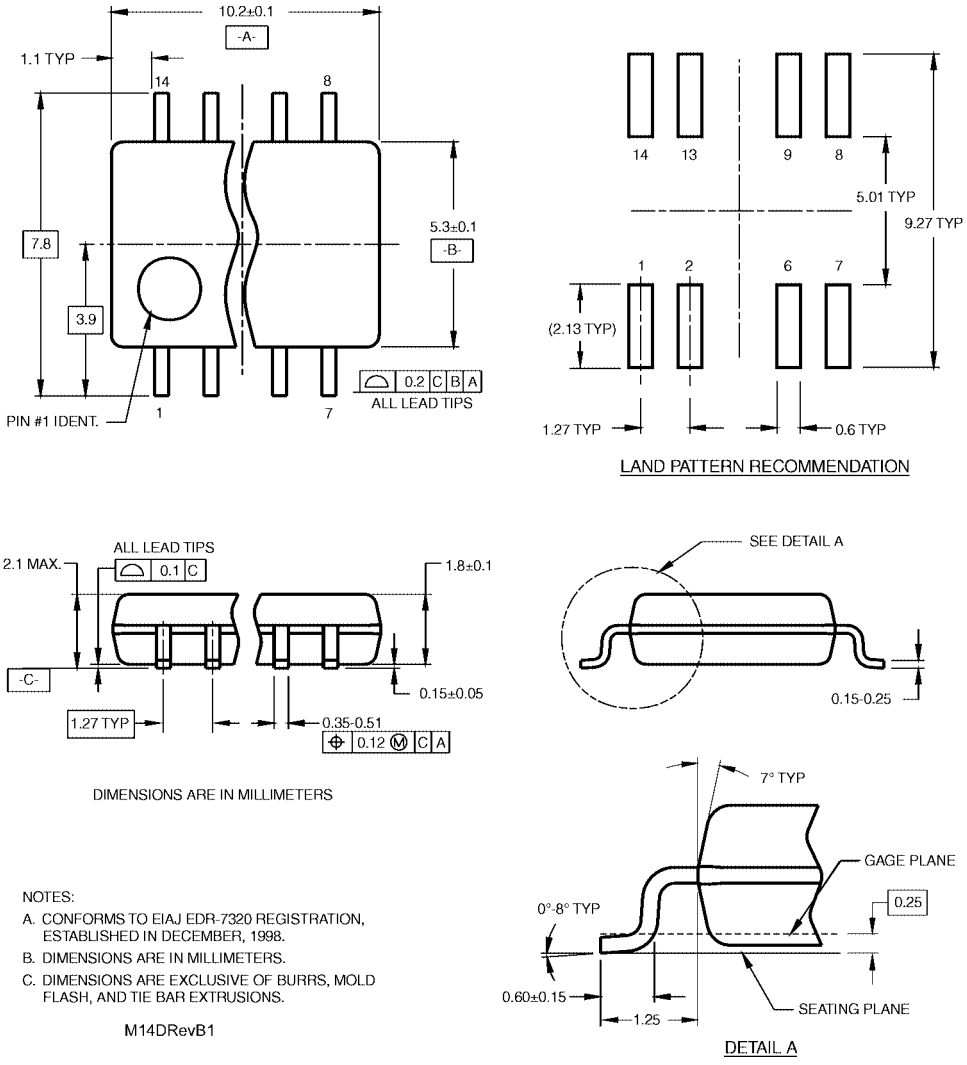
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

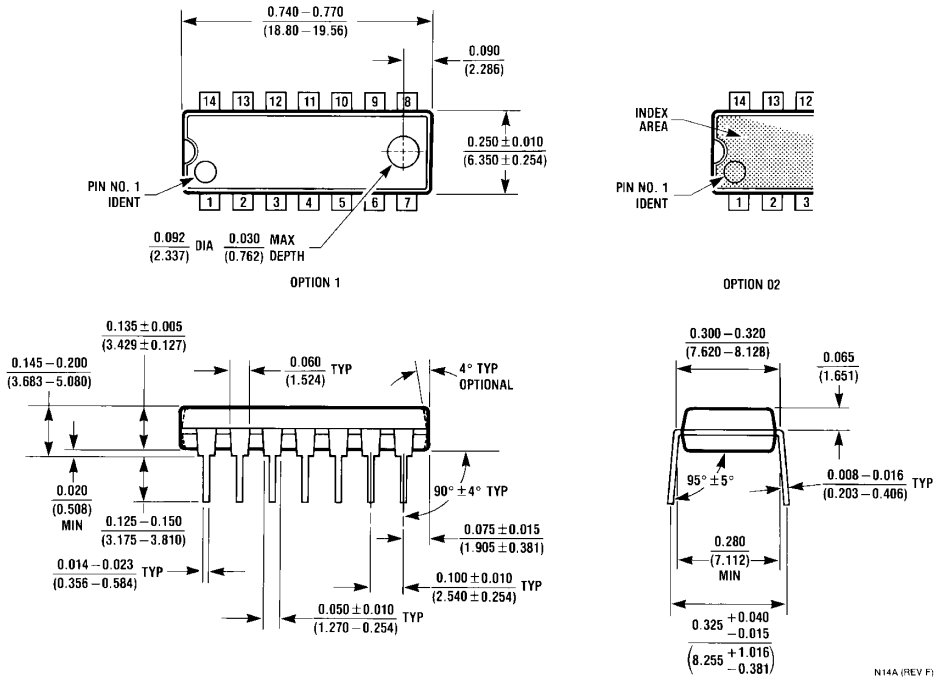
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1990
Revised November 1999

74ACTQ04
Quiet Series™ Hex Inverter

General Description

The ACTQ04 contains six inverters and utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

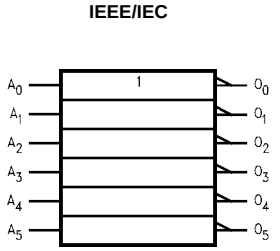
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- Has TTL-compatible inputs

Ordering Code:

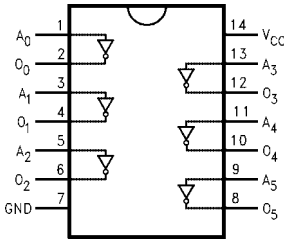
Order Number	Package Number	Package Description
74ACTQ04SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACTQ04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ04PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source	
or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside of databook specifications.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2
							(Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2
							(Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW LevelDynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n−1) inputs switching 0V to 3V Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	2.0	6.5	7.5	2.0	8.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	2.0	6.5	7.5	2.0	8.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	75	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT™.

Equipment:

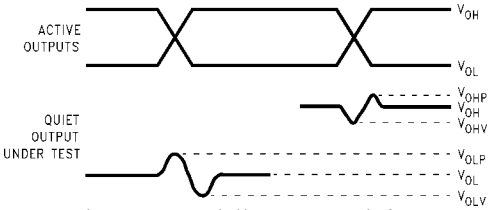
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition.for active and enable
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

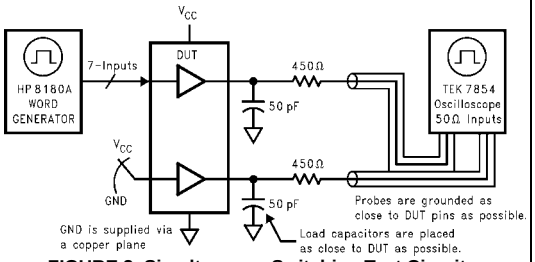
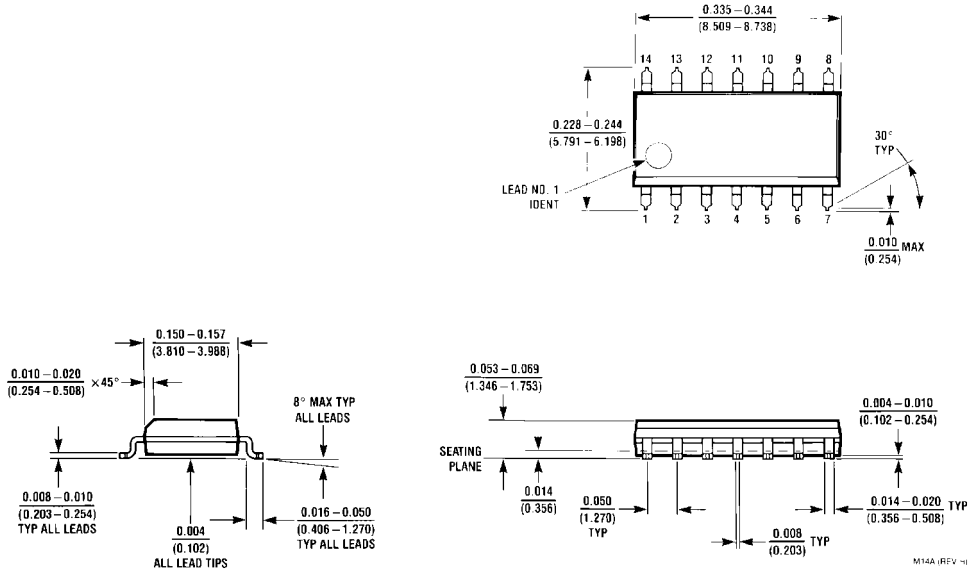


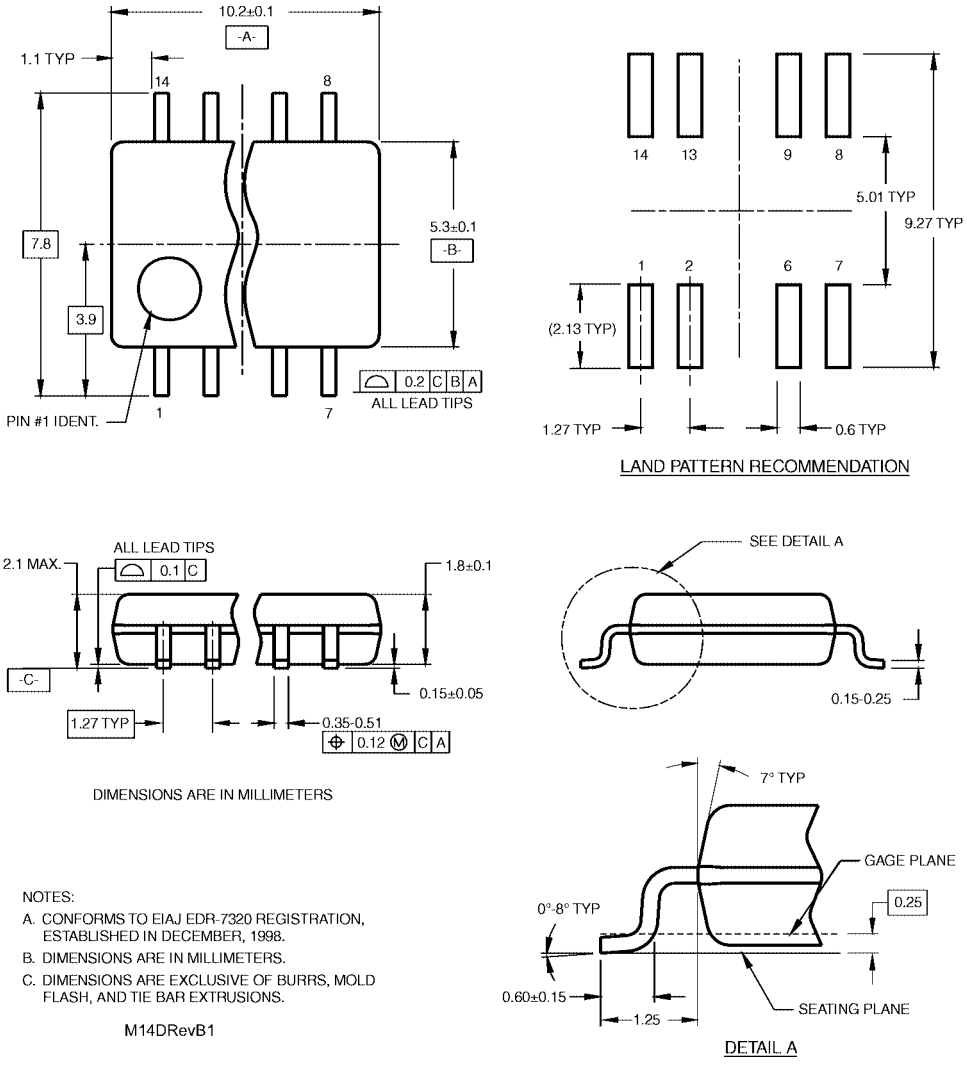
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

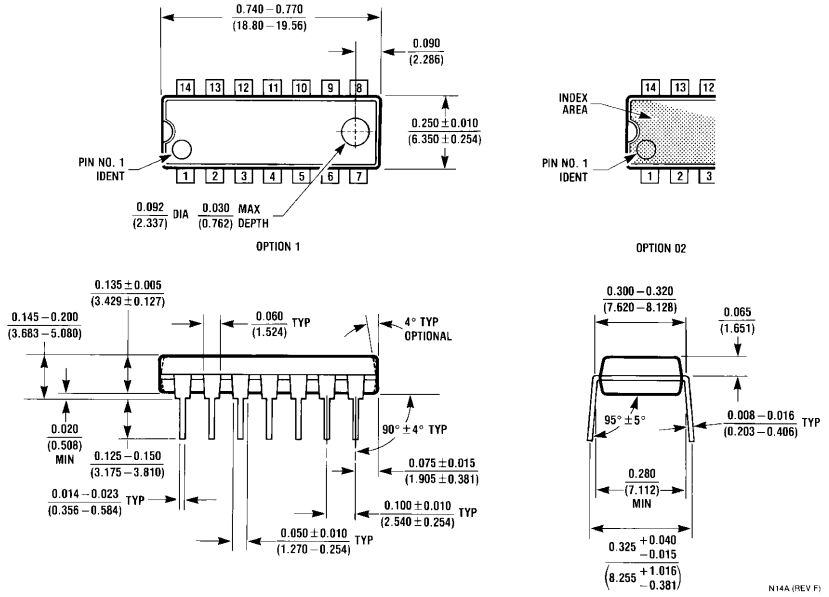
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1990
Revised November 1999

74ACTQ08
Quiet Series™ Quad 2-Input AND Gate

General Description

The ACTQ08 contains four, 2-input AND gates and utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- TTL-compatible inputs

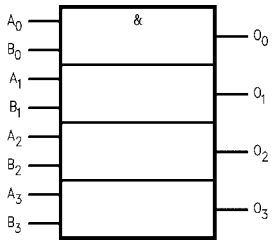
Ordering Code:

Order Number	Package Number	Package Description
74ACTQ08SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
74ACTQ08SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ08PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

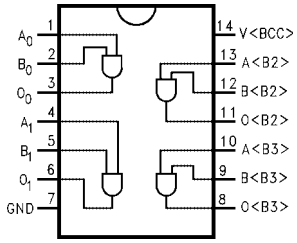
Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside of databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
						V	V_{IN} = V_{IL}or V_{IH}
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n−1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	2.5	6.0	6.5	2.5	7.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	2.5	6.0	6.5	2.5	7.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

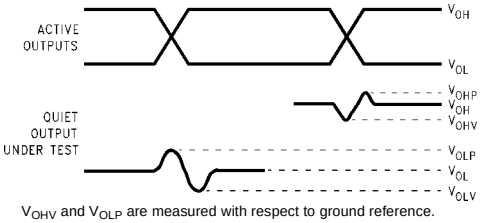
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillator steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

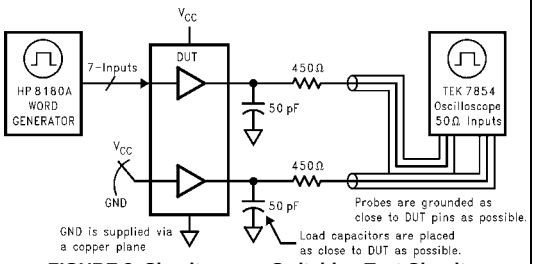
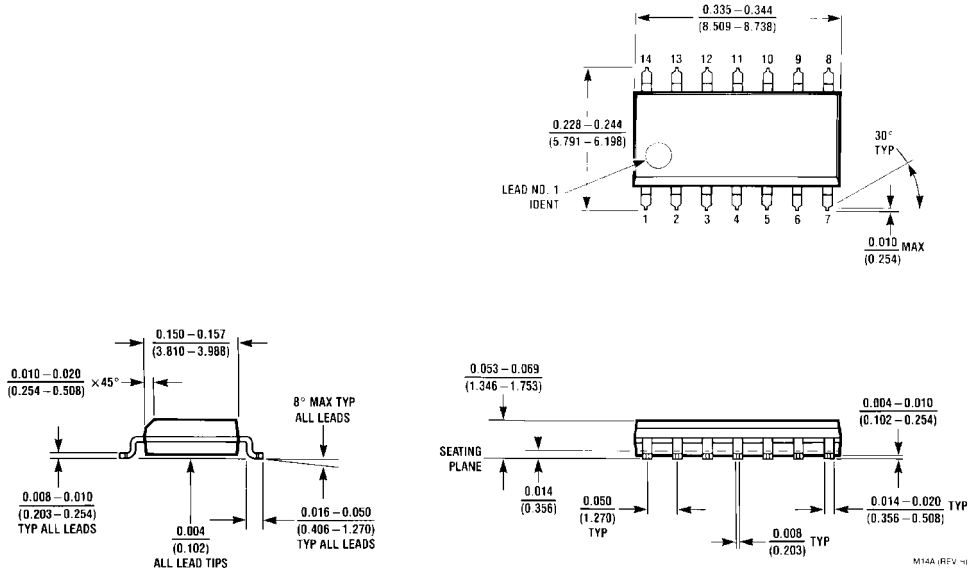


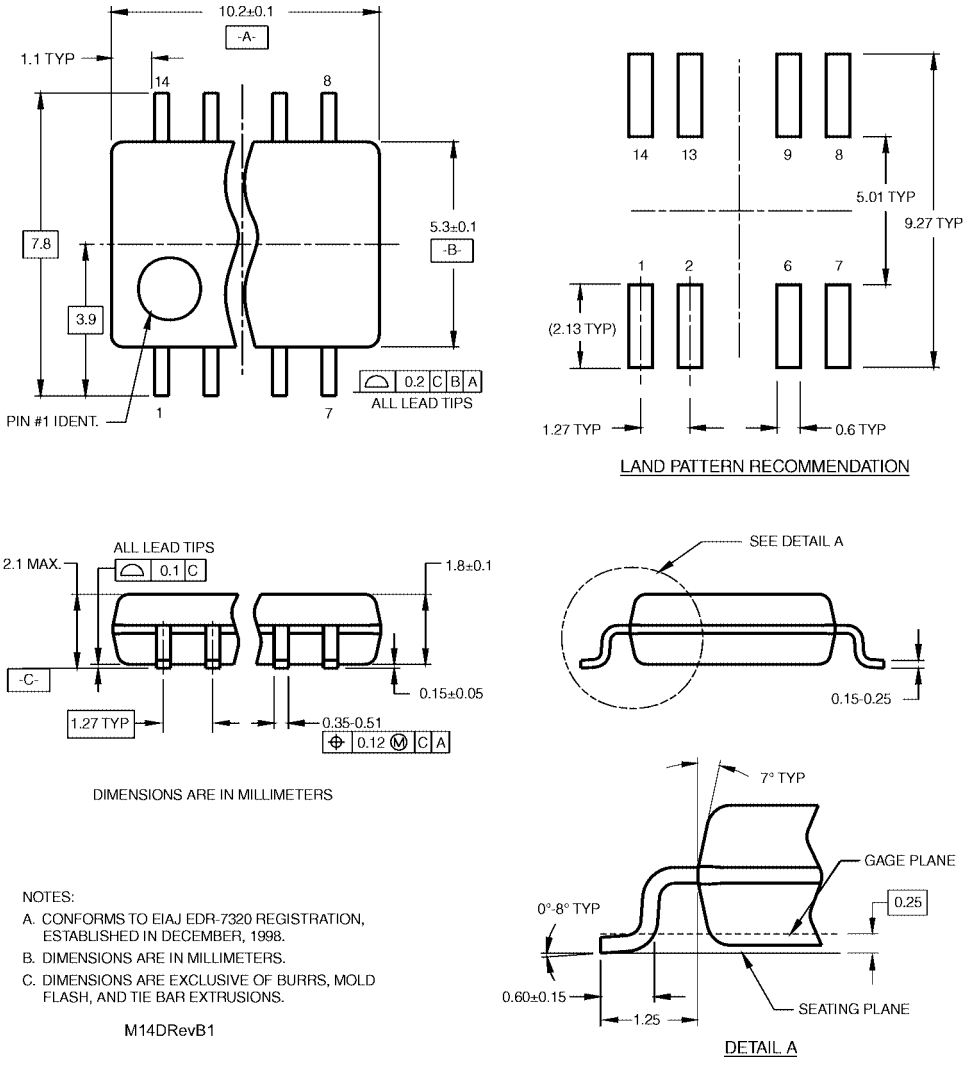
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

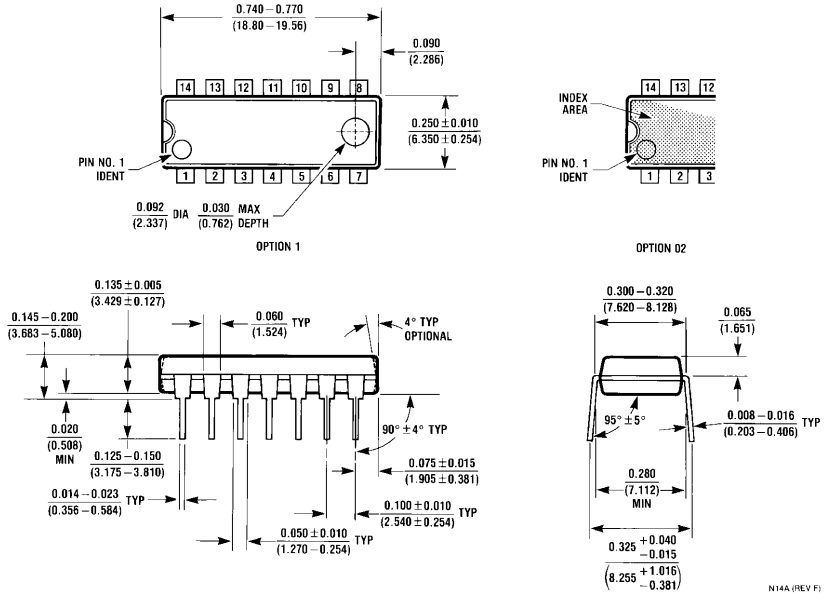
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1990
Revised January 2000

74ACTQ10
Quiet Series™ Triple 3-Input NAND Gate

General Description

The ACTQ10 contains three, 3-input NAND gates and utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- ACTQ 10 has TTL-compatible inputs

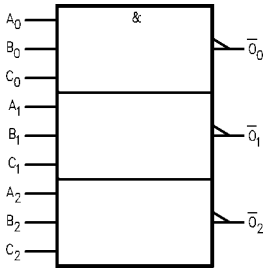
Ordering Code:

Order Number	Package Number	Package Description
74ACTQ10SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74ACTQ10PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

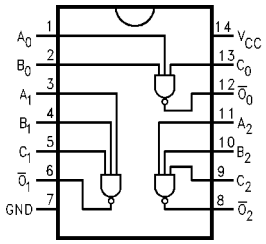
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Descriptions
A_n, B_n, C_n	Inputs
$\overline{O}_n$	Outputs

FACT™, Quiet Seriers™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside of databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = − 24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP Package.

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n-1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHZ.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.0	6.0	7.5	2.0	8.5	ns
t_{PHL}	Propagation Delay	5.0	2.0	6.0	7.5	2.0	8.5	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	85	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT™.

Equipment:

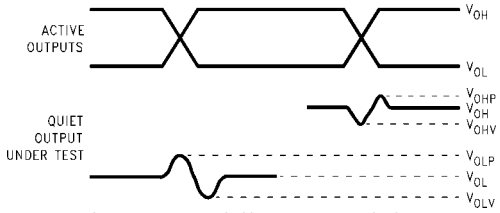
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACTQ devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

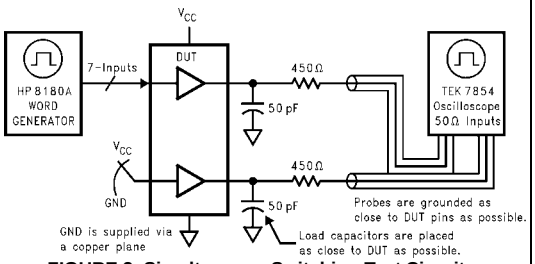
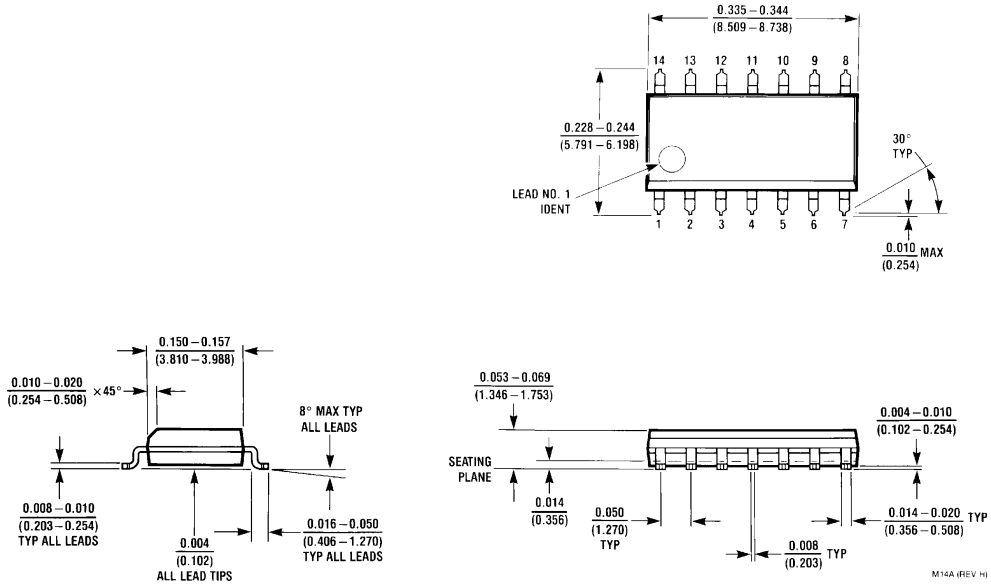


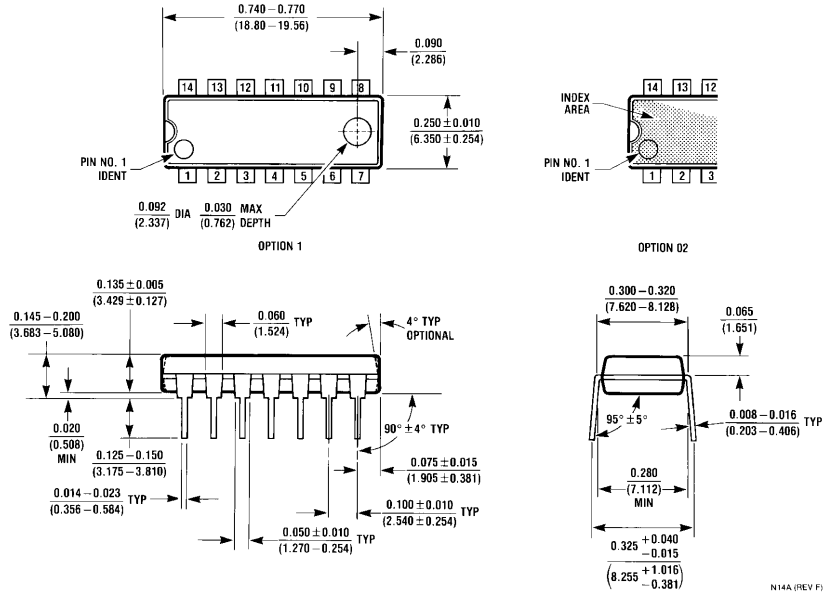
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

March 1991
Revised November 1999

74ACTQ14
Quiet Series™ Hex Inverter with Schmitt Trigger Input

General Description

The ACTQ14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The ACTQ14 utilizes Fairchild Quiet Series™ Technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

The ACTQ14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

Features

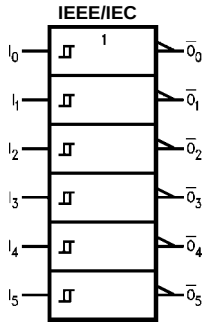
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed pin-to-pin skew AC performance
- Outputs source/sink 24 mA

Ordering Code:

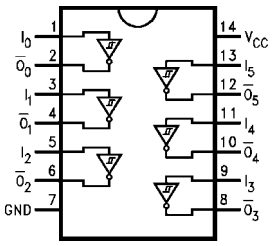
Order Number	Package Number	Package Description
74ACTQ14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ACTQ14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACTQ14PC	N14A	14-Lead Plastic Dual-In-Lead Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
I_n	Inputs
$\overline{O}_n$	Outputs

Function Table

Input	Output
A	$\overline{\mathbf{O}}$
L	H
H	L

Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source	
or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside of databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	V_I = V_{CC}, GND
$V_{h(max)}$	Maximum Hysteresis	4.5		1.4	1.4	V	T_A = Worst Case
		5.5		1.6	1.6		
$V_{h(min)}$	Minimum Hysteresis	4.5		0.4	0.4	V	T_A = Worst Case
		5.5		0.5	0.5		
V_t+	Maximum Positive Threshold	4.5		2.0	2.0	V	T_A = Worst Case
		5.5		2.0	2.0		
V_t−	Minimum Negative Threshold	4.5		0.8	0.8	V	T_A = Worst Case
		5.5		0.8	0.8		
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n–1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	3.0	8.0	10.0	3.0	11.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	3.0	8.0	10.0	3.0	11.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	80	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

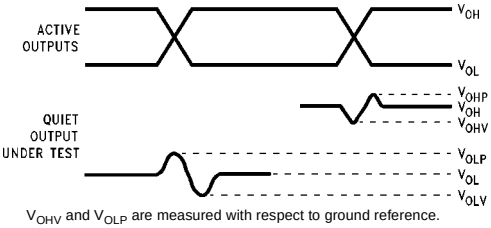
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

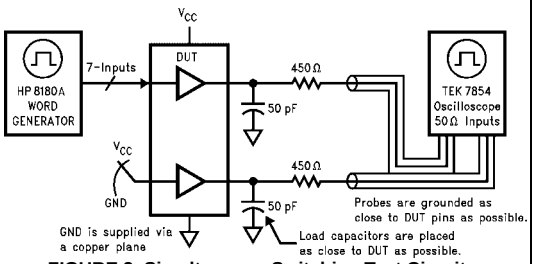
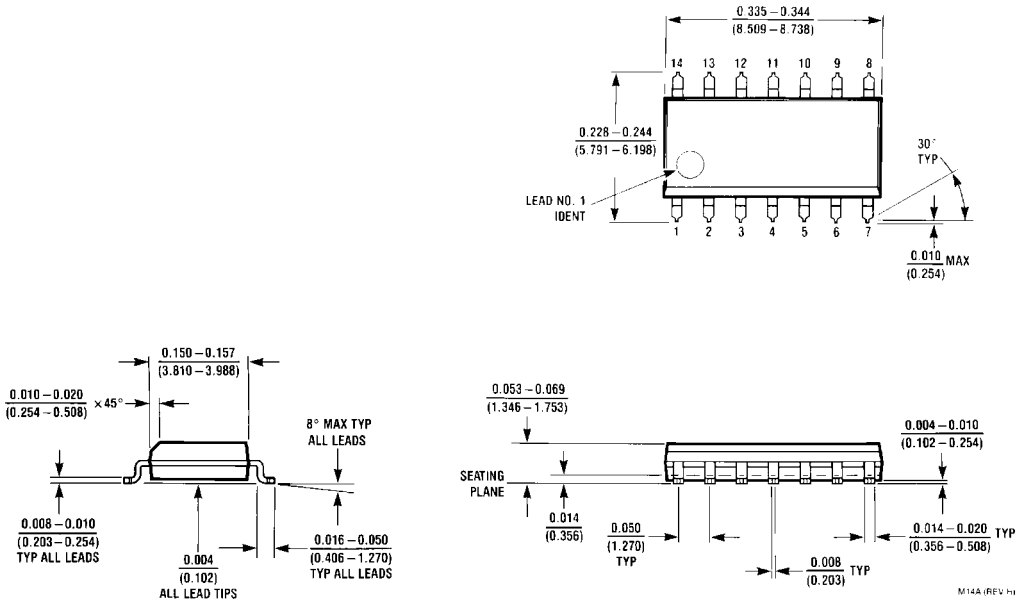


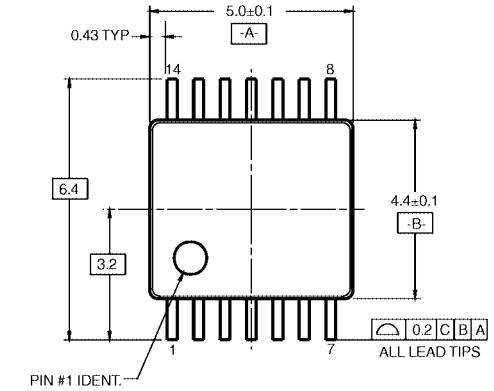
FIGURE 2. Simultaneous Switching Test Circuit

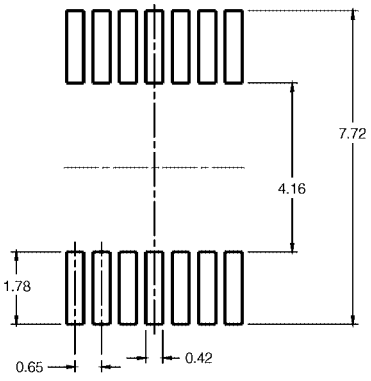
Physical Dimensions inches (millimeters) unless otherwise noted



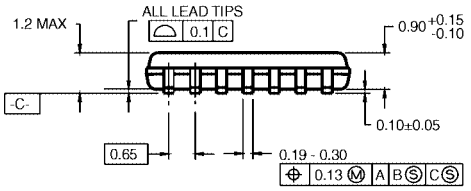
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
Package Number M14A

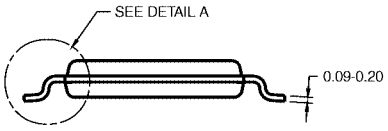
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

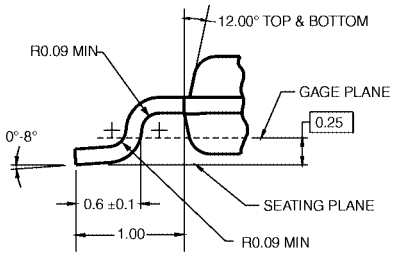




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

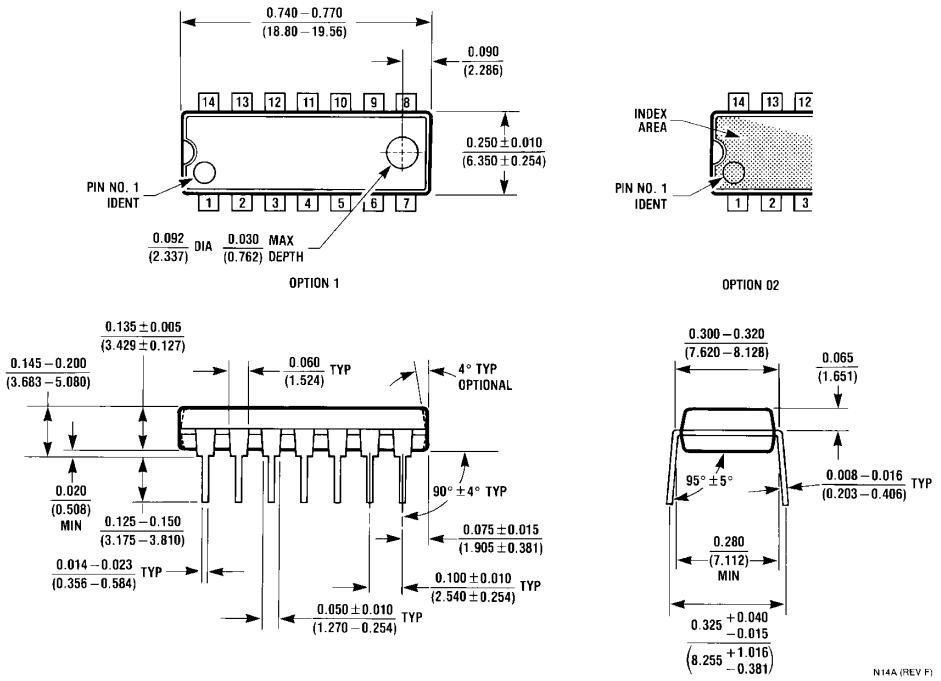
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Lead Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

July 1990
Revised May 1999

74ACTQ153
Quiet Series Dual 4-Input Multiplexer

General Description

The ACTQ153 is a high-speed dual 4-input multiplexer with common select inputs and individual enable inputs for each section. It can select two lines of data from four sources. The two buffered outputs present data in the true (non-inverted) form. In addition to multiplexer operation, the ACTQ153 can act as a function generator and generate any two functions of three variables.

Features

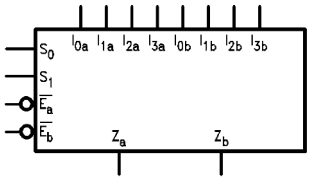
- Outputs source/sink 24 mA
- ACTQ153 has TTL-compatible inputs
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity

Ordering Code:

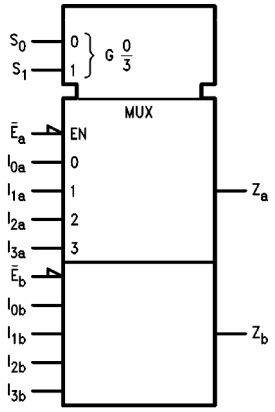
Order Number	Package Number	Package Description
74ACTQ153SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74ACTQ153PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

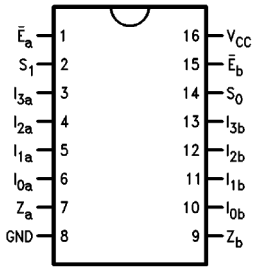
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a} - I_{3a}	Side A Data Inputs
I_{0b} - I_{3b}	Side B Data Inputs
S_0, S_1	Common Select Inputs
$\overline{E}_a$	Side A Enable Input
$\overline{E}_b$	Side B Enable Input
Z_a	Side A Output
Z_b	Side B Output

FACT™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

The ACTQ153 is a dual 4-input multiplexer. It can select two bits of data from up to four sources under the control of the common Select inputs (S_0, S_1). The two 4-input multiplexer circuits have individual active-LOW Enables ($\overline{E}_a$, $\overline{E}_b$) which can be used to strobe the outputs independently. When the Enables ($\overline{E}_a$, $\overline{E}_b$) are HIGH, the corresponding outputs (A_z, Z_b) are forced LOW. The ACTQ153 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the Select inputs. The logic equations for the outputs are shown below.

$$Z_a = \overline{E}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0)$$

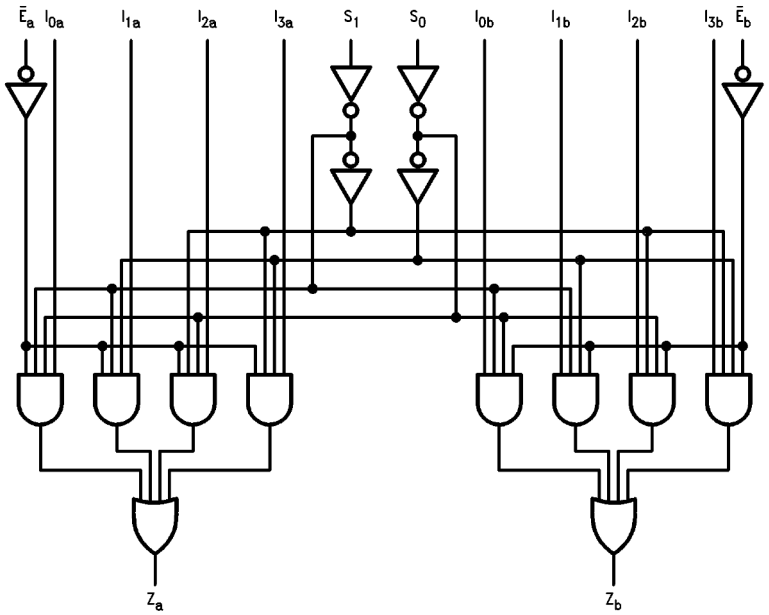
$$Z_b = \overline{E}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 \bullet I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet \overline{S}_0 + I_{3b} \bullet S_1 \bullet S_0)$$

Truth Table

Select Inputs		Inputs (a or b)					Outputs
S_0	S_1	$\overline{E}$	I_0	I_1	I_2	I_3	Z
X	X	H	X	X	X	X	L
L	L	L	L	X	X	X	L
L	L	L	H	X	X	X	H
H	L	L	X	L	X	X	L
H	L	L	X	H	X	X	H
L	H	L	X	X	L	X	L
L	H	L	X	X	H	X	H
H	H	L	X	X	X	L	L
H	H	L	X	X	X	H	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	μA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Maximum HIGH Level Output Noise	5.0	1.1	1.5		V	Figure 1Figure 2 (Note 4)(Note 5)
V_{OLV}	Maximum LOW Level Output Noise	5.0	−0.6	−1.2		V	Figure 1Figure 2
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

DC Electrical Characteristics (Continued)

Note 4: Worst case package.

Note 5: Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One Data Input @ V_{IN} = GND.

Note 6: Max number of Data Inputs (n) switching. (n–1) inputs switching 0V to 5V. Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay S_n to Z_n	5.0	3.0	7.0	11.5	2.0	13.5	ns
t_{PHL}	Propagation Delay S_n to Z_n	5.0	3.0	7.0	11.5	2.5	13.5	ns
t_{PLH}	Propagation Delay $\overline{E}_n$ to Z_n	5.0	2.0	6.5	10.5	2.0	12.5	ns
t_{PHL}	Propagation Delay $\overline{E}_n$ to Z_n	5.0	3.0	6.0	9.5	2.5	11.0	ns
t_{PLH}	Propagation Delay I_n to Z_n	5.0	2.5	5.5	9.5	2.0	11.0	ns
t_{PHL}	Propagation Delay I_n to Z_n	5.0	2.0	5.5	9.5	2.0	11.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	65.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

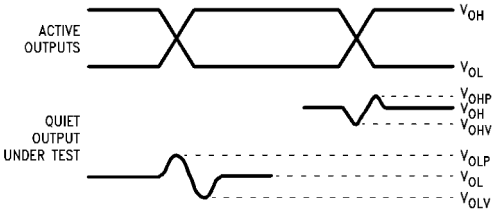
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 8: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 9: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

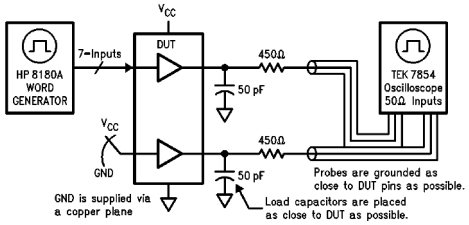
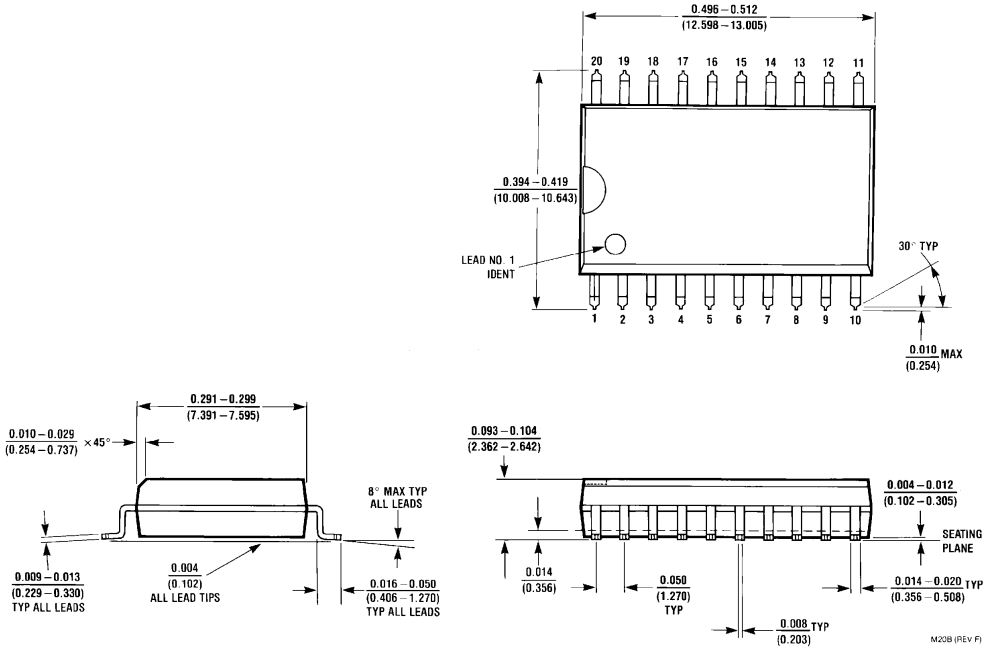


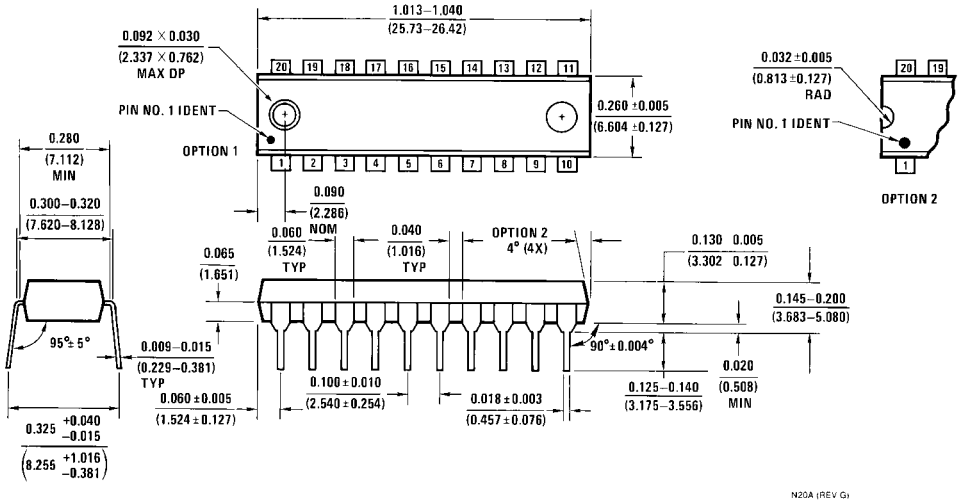
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

May 1991
Revised November 1998

74ACTQ16240
16-Bit Inverting Buffer/Line Driver with 3-STATE Outputs

General Description

The ACTQ16240 contains sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The ACTQ16240 utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

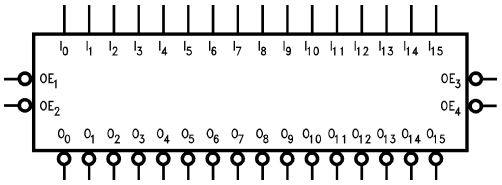
- Utilizes Fairchild's FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte
- 16-bit version of the ACTQ240
- Outputs source/sink 24 mA
- Additional specs for multiple output switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ16240SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

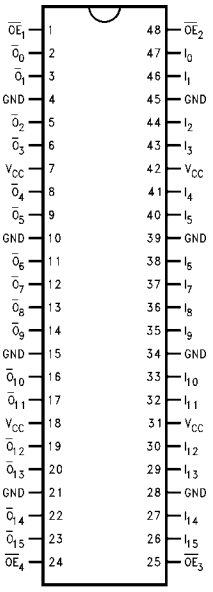


Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active Low)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

Connection Diagram

Pin Assignment for SSOP and TSSOP



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Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

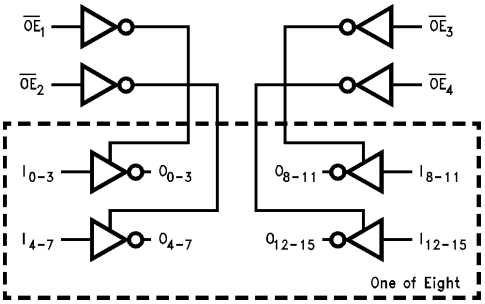
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The ACTQ16240 contains sixteen inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independently of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin	± 50 mA
Junction Temperature	+140°C
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum High	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum Low	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum High	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum Low	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output	5.0	0.5	0.8		V	Figure 1Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−1.0		V	Figure 1Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum High Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum Low Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Maximum number of data inputs (n) switching. (n − 1) input switching 0V to 3V. Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.7	4.8	7.3	2.7	7.8	ns
t_{PHL}	Data to Output		3.0	5.1	7.3	3.0	7.8	
t_{PZH}	Output Enable Time	5.0	2.5	4.5	7.4	2.5	7.9	ns
t_{PZL}			2.7	4.7	7.5	2.7	8.0	
t_{PHZ}	Output Disable Time	5.0	2.3	5.0	7.9	2.3	8.2	ns
t_{PLZ}			2.0	4.6	7.4	2.0	7.9	

Note 8: Voltage Range 5.0 is 5.0V ±0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, V_{CC} = Com, $C_L = 50$ pF, 16 Outputs Switching (Note 10)			$T_A = -40°C$ to $+85°C$, V_{CC} = Com, $C_L = 250$ pF (Note 11)		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0		11.2	5.6	13.8	ns
t_{PHL}	Data to Output	4.0		10.0	5.6	13.6	
t_{PZH}	Output Enable Time	3.5		10.1	(Note 12)		ns
t_{PZL}		3.4		10.0			
t_{PHZ}	Output Disable Time	3.6		8.9	(Note 13)		ns
t_{PLZ}		3.1		8.1			
t_{OSHL} (Note 9)	Pin to Pin Skew HL Data to Output			1.2			ns
t_{OSLH} (Note 9)	Pin to Pin Skew LH Data to Output			2.5			ns
t_{OST} (Note 9)	Pin to Pin Skew LH/HL Data to Output			4.3			ns

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}).

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all low-to-high, high-to-low, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 13: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.

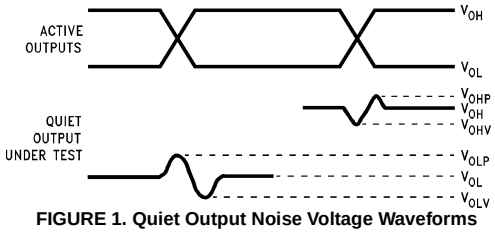


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 14: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 15: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level on the, V_{IH}, until the output begins to oscillate or steps out a mins of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

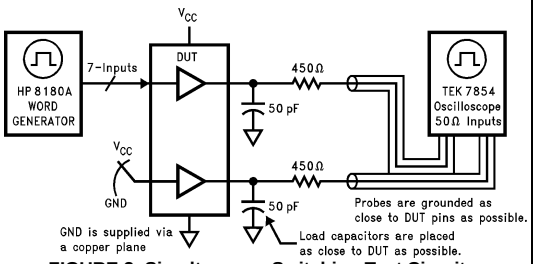
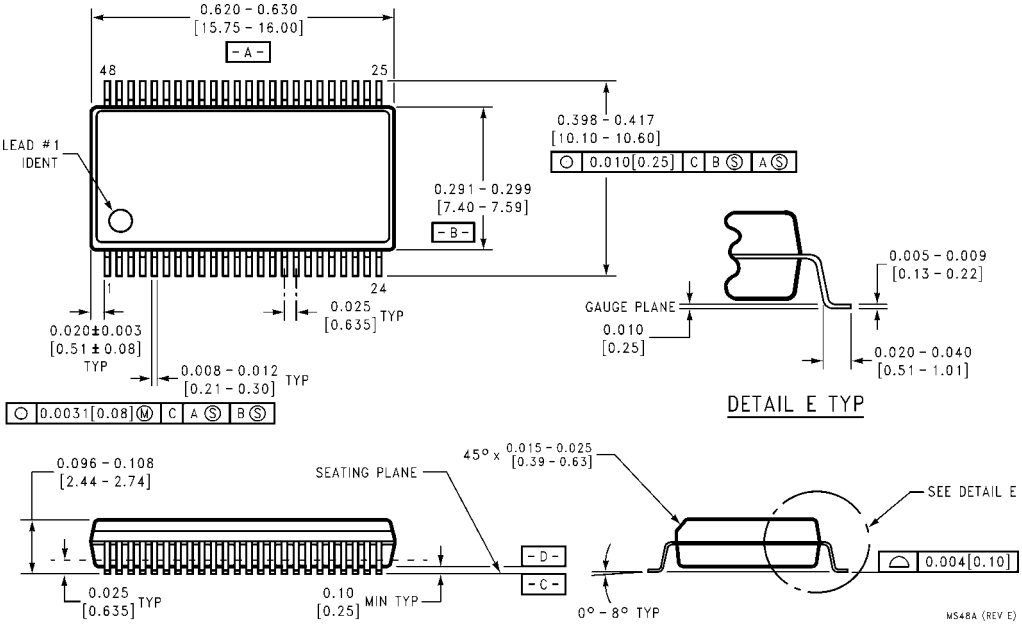


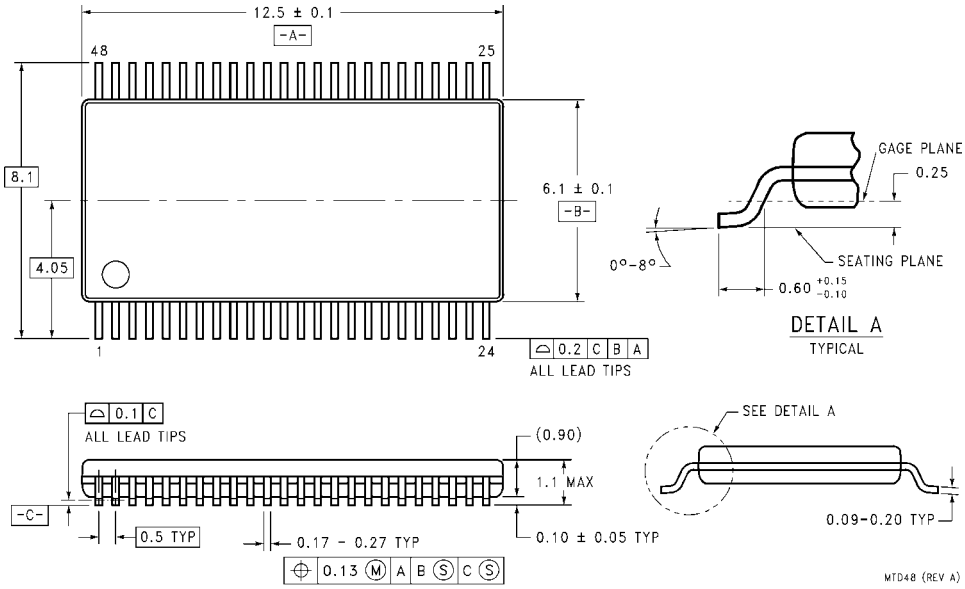
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Think Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

May 1991
Revised November 1999

74ACTQ16244
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACTQ16244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The ACTQ16244 utilizes Fairchild's Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

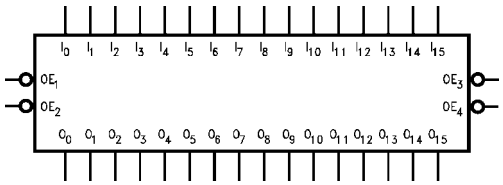
- Utilizes Fairchild's FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte and nibble
- 16-bit version of the ACTQ244
- Outputs source/sink 24 mA
- Additional specs for multiple output switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ16244SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

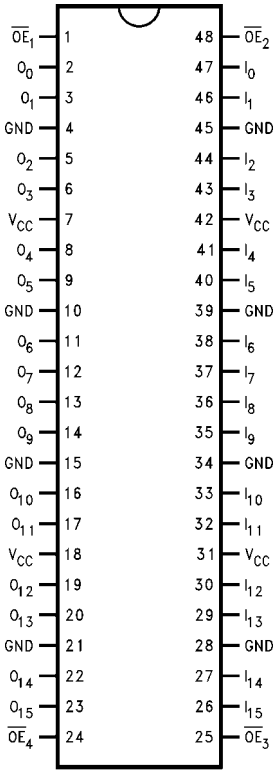


Pin Description

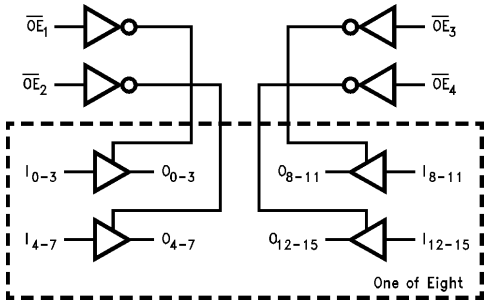
Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

FACT™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Connection Diagram



Logic Diagram



Functional Description

The ACTQ16244 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin	±50 mA
Junction Temperature	+140°C
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OH} = 24 mA
		5.5		0.36	0.44		I_{OH} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND (Note 6)
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−1.0		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	(Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	(Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Max number of data inputs (n) switching. (n − 1) input switching 0V to 3V input under test switching 3V to threshold (V_{ILD})

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation		3.0	5.2	7.3	3.0	7.8	ns
t_{PHL}	Delay A_n, B_n to B_n, A_n	5.0	2.5	4.8	6.8	2.5	7.3	
t_{PZH}	Output Enable	5.0	2.5	5.0	7.4	2.5	7.9	ns
t_{PZL}	Time		2.7	4.6	7.5	2.7	8.0	
t_{PHZ}	Output Disable	5.0	2.3	5.0	7.9	2.3	8.2	ns
t_{PLZ}	Time		2.0	4.6	7.4	2.0	7.9	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, 16 Outputs Switching (Note 11)			$T_A = -40°C$ to $+85°C$, $C_L = 250$ pF (Note 12)		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	4.0		11.6	5.6	14.3	ns
t_{PHL}	Data to Output		3.4		9.6	4.8	13.1	
t_{PZH}	Output Enable	5.0	3.5		10.1	(Note 13)		ns
t_{PZL}	Time		3.4		10.0			
t_{PHZ}	Output Disable	5.0	3.6		8.9	(Note 14)		ns
t_{PLZ}	Time		3.1		8.1			
t_{OSHL} (Note 10)	Pin to Pin Skew HL Data to Output	5.0			1.2			ns
t_{OSLH} (Note 10)	Pin to Pin Skew LH Data to Output	5.0			2.5			ns
t_{OST} (Note 10)	Pin to Pin Skew LH/HL Data to Output	5.0			4.3			ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 13: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 14: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

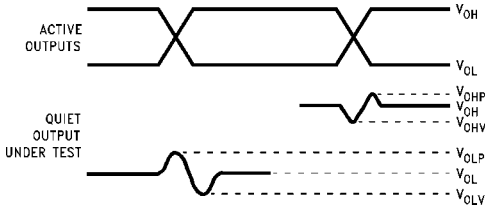
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements

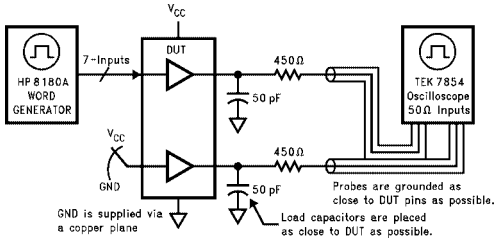
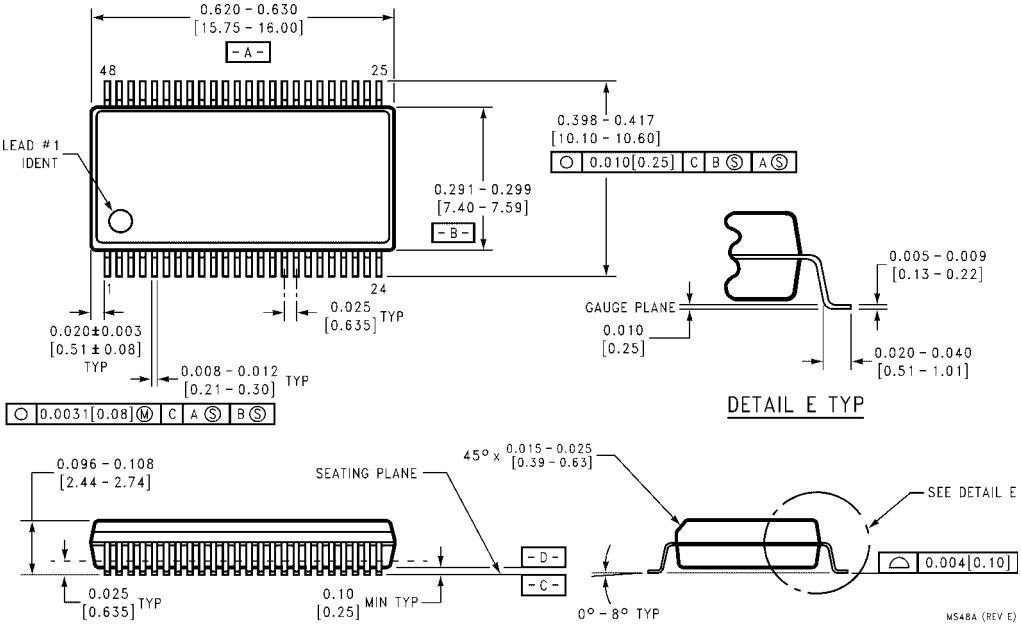


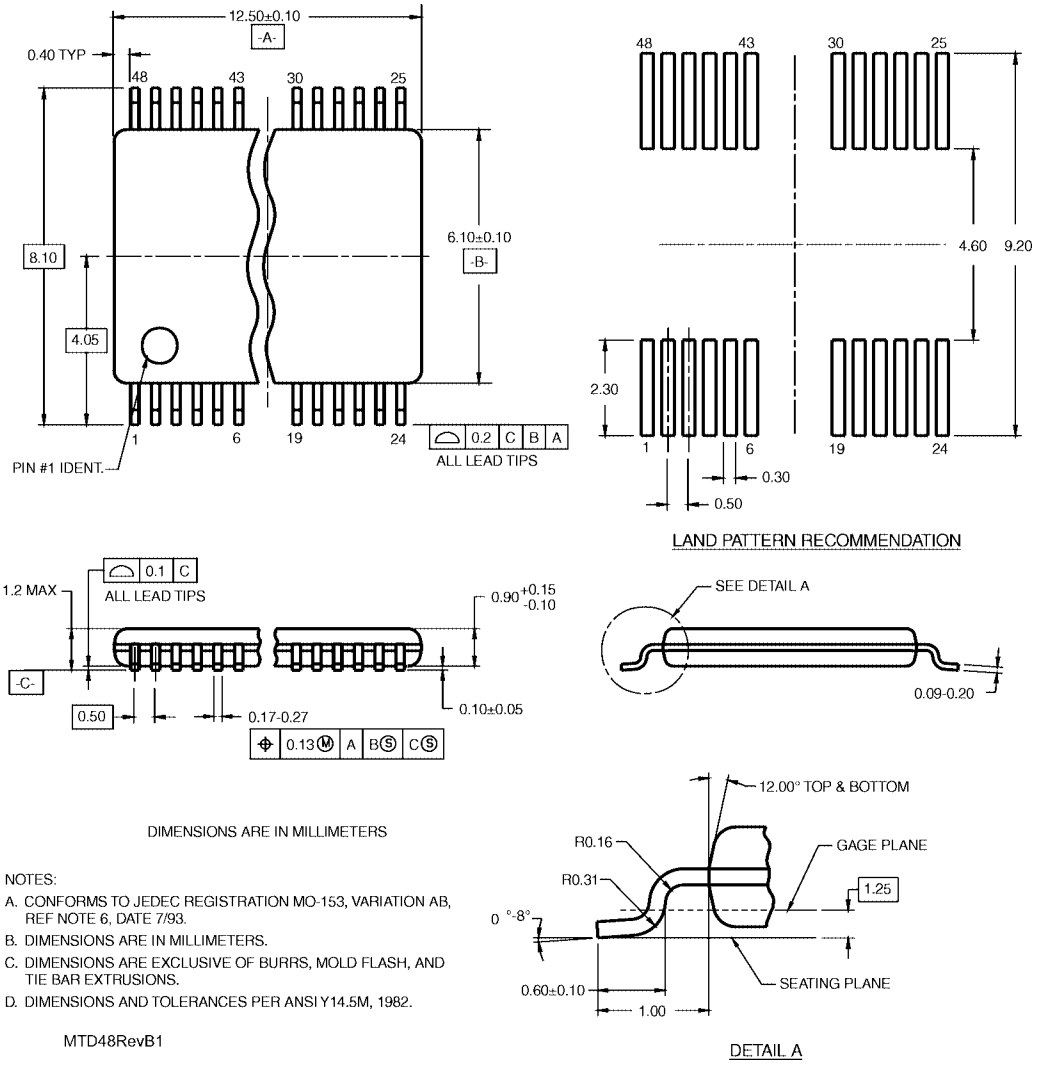
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1991
Revised November 1999

74ACTQ16245
16-Bit Transceiver with 3-STATE Outputs

General Description

The ACTQ16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The ACTQ16245 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

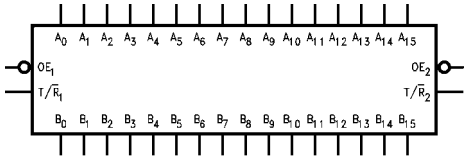
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Bidirectional non-inverting buffers
- Separate control logic for each byte
- 16-bit version of the ACTQ245
- Outputs source/sink 24 mA
- Additional specs for multiple output switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

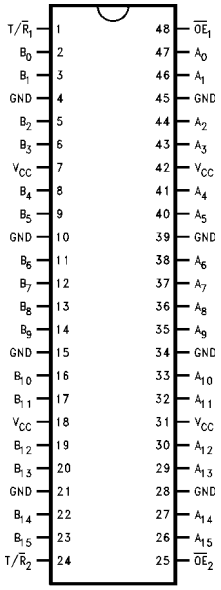
Order Number	Package Number	Package Description
74ACTQ16245SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs/Outputs
B_0–B_{15}	Side B Outputs/Inputs

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Functional Description

The ACTQ16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the $T/\overline{R}$ input is HIGH, then Bus A data is transmitted to Bus B. When the $T/\overline{R}$ input is LOW, Bus B data is transmitted to Bus A. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

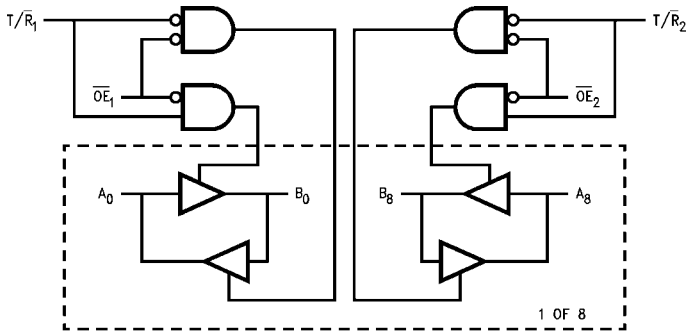
Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH-Z State on A_0–A_7, B_0–B_7

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH-Z State on A_8–A_{15}, B_8–B_{15}

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} +0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin	± 50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to+85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZT}	Maximum I/O Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−0.85		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Max number of data inputs (n) switching. (n − 1) input switching 0V to 3V input under test switching 3V to threshold (V_{ILD})

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	3.2	5.7	8.4	3.2	9.0	ns
t_{PHL}	A_n, B_n to B_n, A_n	5.0	2.6	5.1	7.9	2.6	8.4	
t_{PZH}	Output Enable	5.0	3.7	6.4	9.4	2.7	10.0	ns
t_{PZL}	Time	5.0	4.1	7.4	10.5	3.4	11.6	
t_{PHZ}	Output Disable	5.0	2.2	5.4	8.7	2.2	9.3	ns
t_{PLZ}	Time	5.0	2.0	5.2	8.2	2.0	8.8	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, 16 Outputs Switching (Note 11)			$T_A = -40°C$ to $+85°C$, $C_L = 250$ pF (Note 12)		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	4.2		11.9	5.9	14.6	ns
t_{PHL}	Data to Output	5.0	3.5		9.9	5.0	13.4	
t_{PZH}	Output Enable Time	5.0	4.5		11.4	(Note 13)		ns
t_{PZL}		5.0	4.4		12.2			
t_{PHZ}	Output Disable Time	5.0	3.5		9.3	(Note 14)		ns
t_{PZL}		5.0	3.1		8.8			
t_{OSHL} (Note 10)	Pin to Pin Skew HL Data to Output	5.0			1.2			ns
t_{OSLH} (Note 10)	Pin to Pin Skew LH Data to Output	5.0			1.3			ns
t_{OST} (Note 10)	Pin to Pin Skew LH/HL Data to Output	5.0			3.0			ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 13: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 14: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	25	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

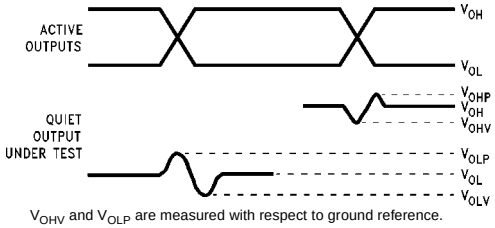
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

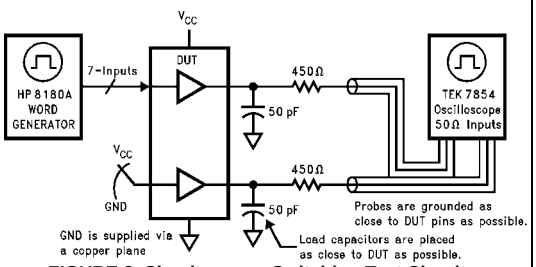
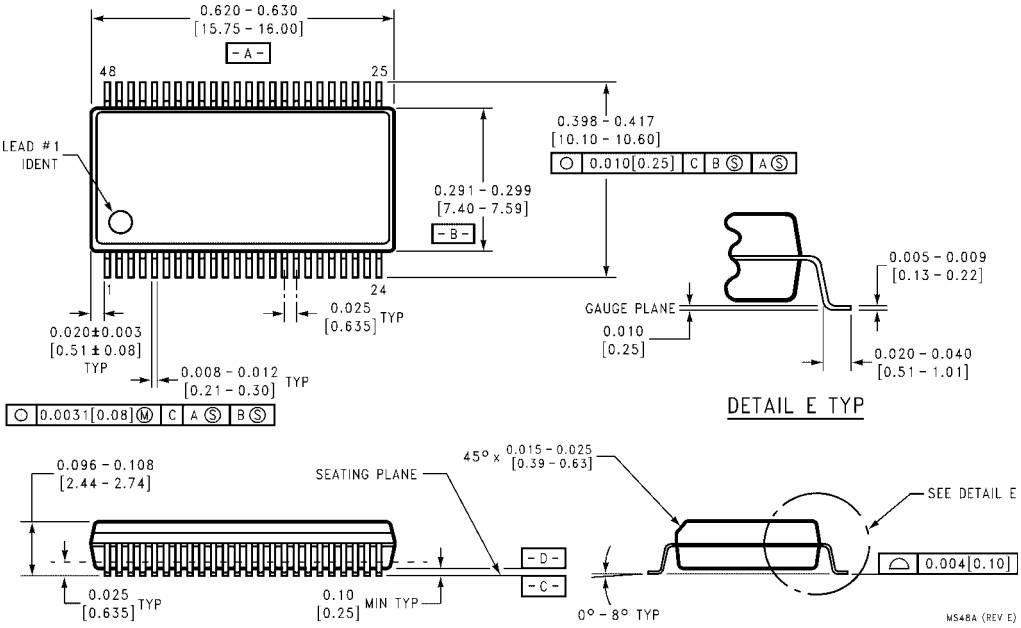


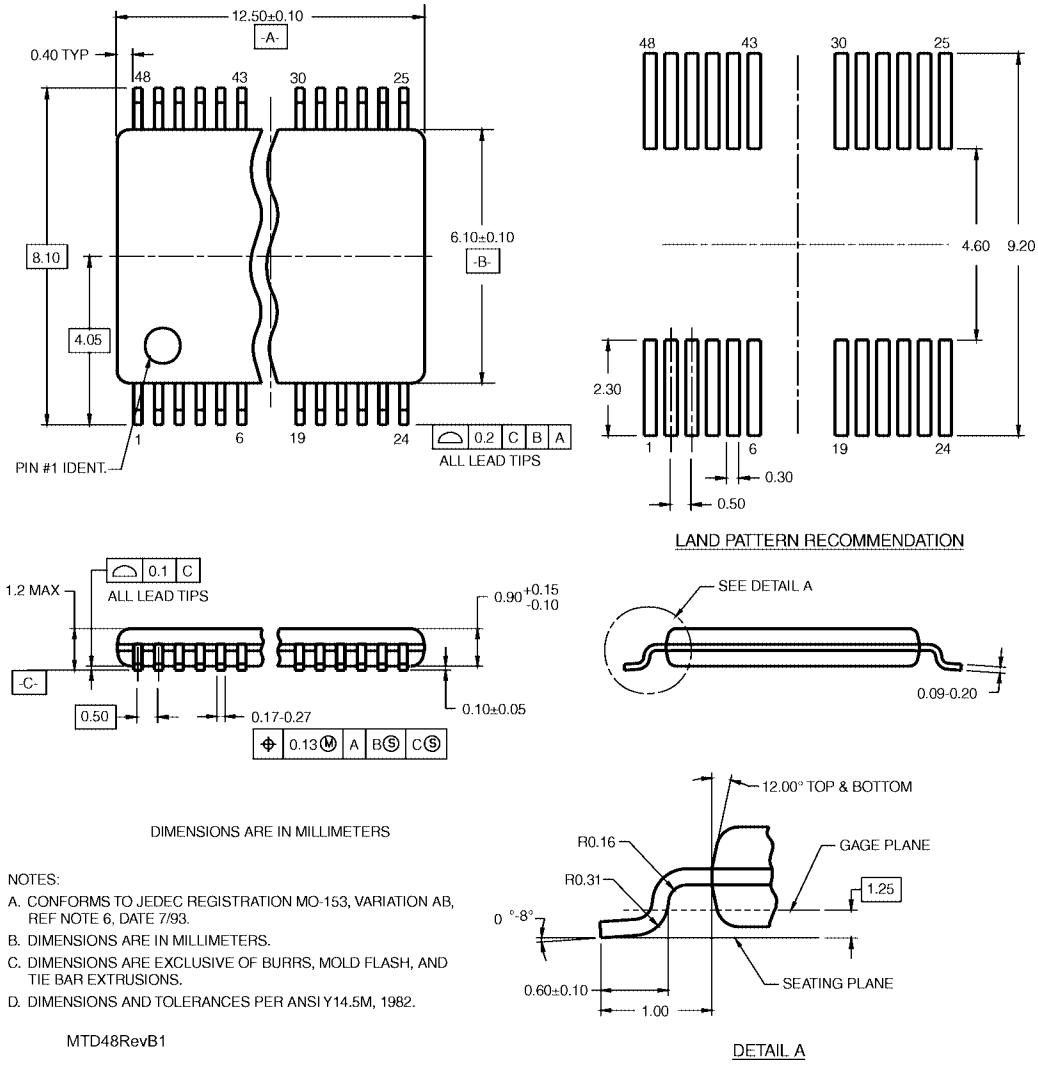
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1991
Revised November 1999

74ACTQ16373
16-Bit Transparent Latch with 3-STATE Outputs

General Description

The ACTQ16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is low, the data that meets the setup time is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the outputs are in high Z state. The ACTQ16373 utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

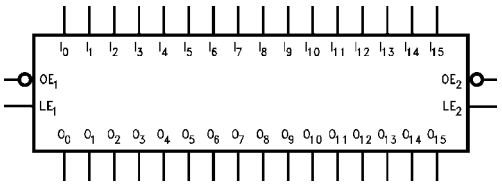
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte
- 16-bit version of the ACTQ373
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output Loading specs for both 50 pF and 250 pF loads

Ordering Code:

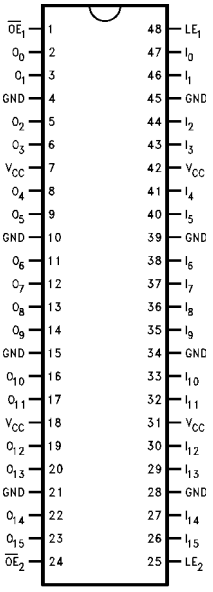
Order Number	Package Number	Package Description
74ACTQ16373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

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Functional Description

The ACTQ16373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the D_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change states each time its D input changes. When LE_n is LOW, the latches store information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

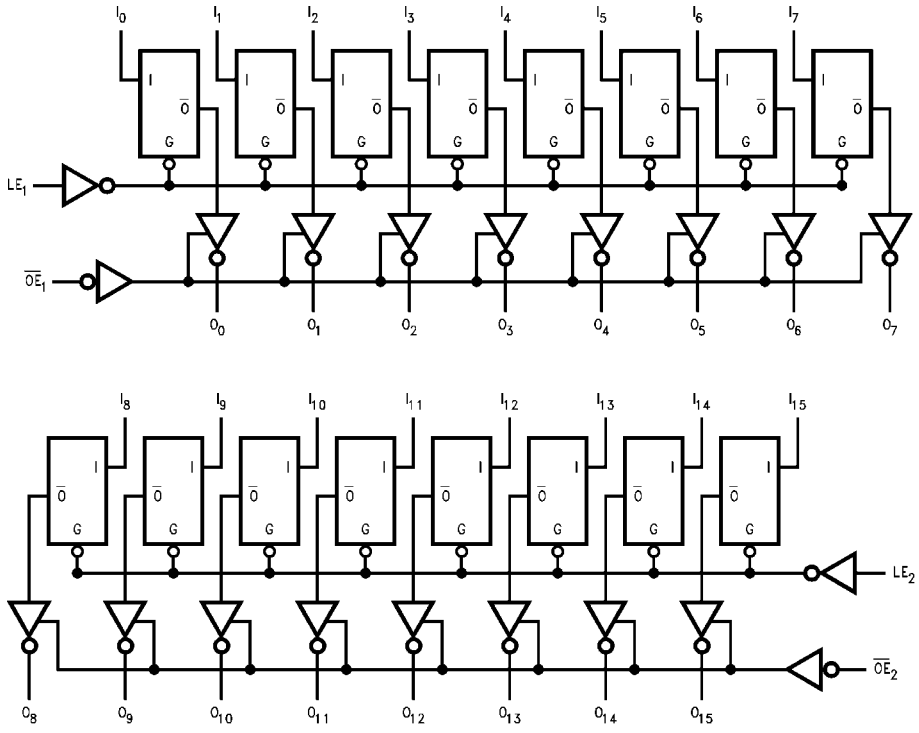
Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	(Previous)

Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	(Previous)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
Previous = previous output prior to HIGH-to-LOW transition of LE

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	+50 mA
DC V_{CC} or Ground Current per Output Pin	+50 mA
Junction Temperature	+140°C
Storage Temperature	−65°C to+150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76		I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44		I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−1.0		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Max number of data inputs (n) switching, (n − 1) input switching 0V to 3V. Input under test switching 3V to threshold (V_{ILD})

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	3.1	5.3	7.9	3.1	8.4	ns
t_{PHL}	D_n to O_n		2.6	4.6	7.3	2.6	7.8	
t_{PLH}	Propagation Delay	5.0	3.1	5.4	7.9	3.2	8.4	ns
t_{PHL}	LE to O_n		2.8	4.9	7.3	2.8	7.8	
t_{PZH}	Output Enable	5.0	2.5	4.7	7.4	2.5	7.9	ns
t_{PZL}	Delay		2.7	4.8	7.5	2.7	8.0	
t_{PHZ}	Output Disable	5.0	2.1	5.1	7.9	2.1	8.2	ns
t_{PLZ}	Delay		2.0	4.5	7.4	2.0	7.9	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, 16 Outputs Switching (Note 10)		$T_A = -40°C$ to $+85°C$, $C_L = 250$ pF (Note 11)		Units
			Min	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0V	4.7	12.7	6.6	15.7	ns
t_{PHL}	Data to Output		4.6	10.6	6.4	14.5	
t_{PLH}	Propagation Delay	5.0V	4.6	13.3	6.3	15.3	ns
t_{PHL}	Latch Enable to Output		4.1	10.4	5.8	13.6	
t_{PZH}	Output Enable	5.0V	3.5	10.4	(Note 12)		ns
t_{PZL}	Time		3.6	10.9			
t_{PHZ}	Output Disable	5.0V	3.4	8.5	(Note 13)		ns
t_{PLZ}	Time		3.1	8.1			
t_{OSHL} (Note 14)	Pin to Pin Skew HL Data to Output	5.0V		1.3			ns
t_{OSLH} (Note 14)	Pin to Pin Skew LH Data to Output	5.0V		2.1			ns
t_{OST} (Note 14)	Pin to Pin Skew LH/HL Data to Output	5.0V		4.0			ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 13: The Output Disable Time is dominated by the RC Network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 15)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW, Input to Clock	5.0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW Input to Clock	5.0	1.5	1.5	ns
t_W	CS Pulse Width, HIGH or LOW	5.0	4.0	4.0	ns

Note 15: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

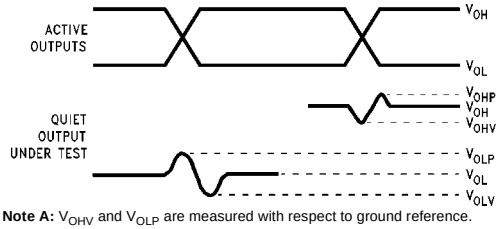
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note A: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note B: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV}on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH} until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

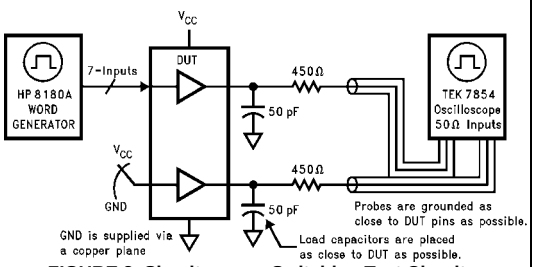
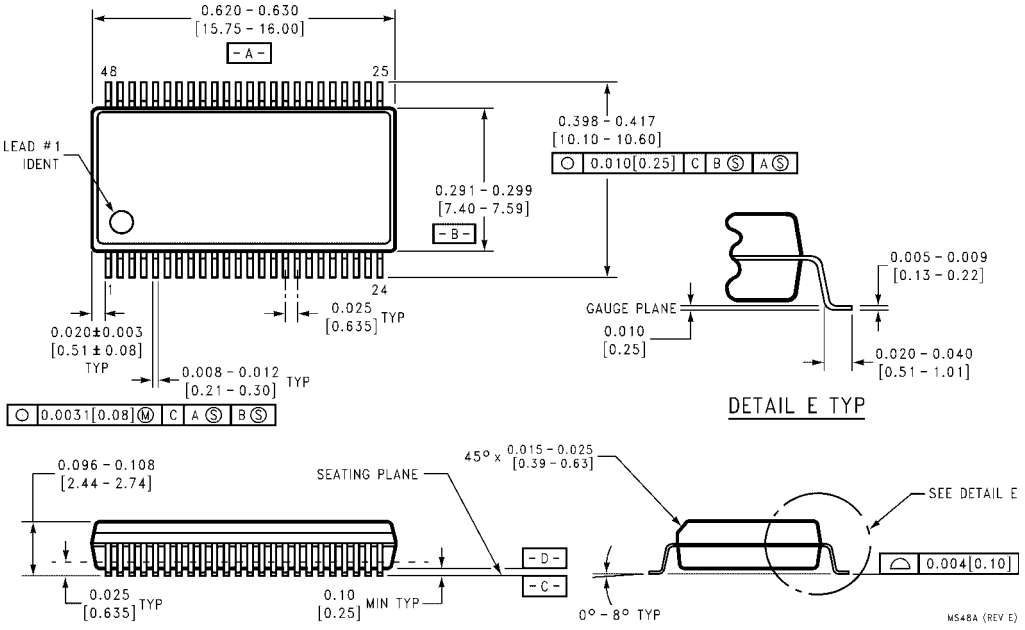


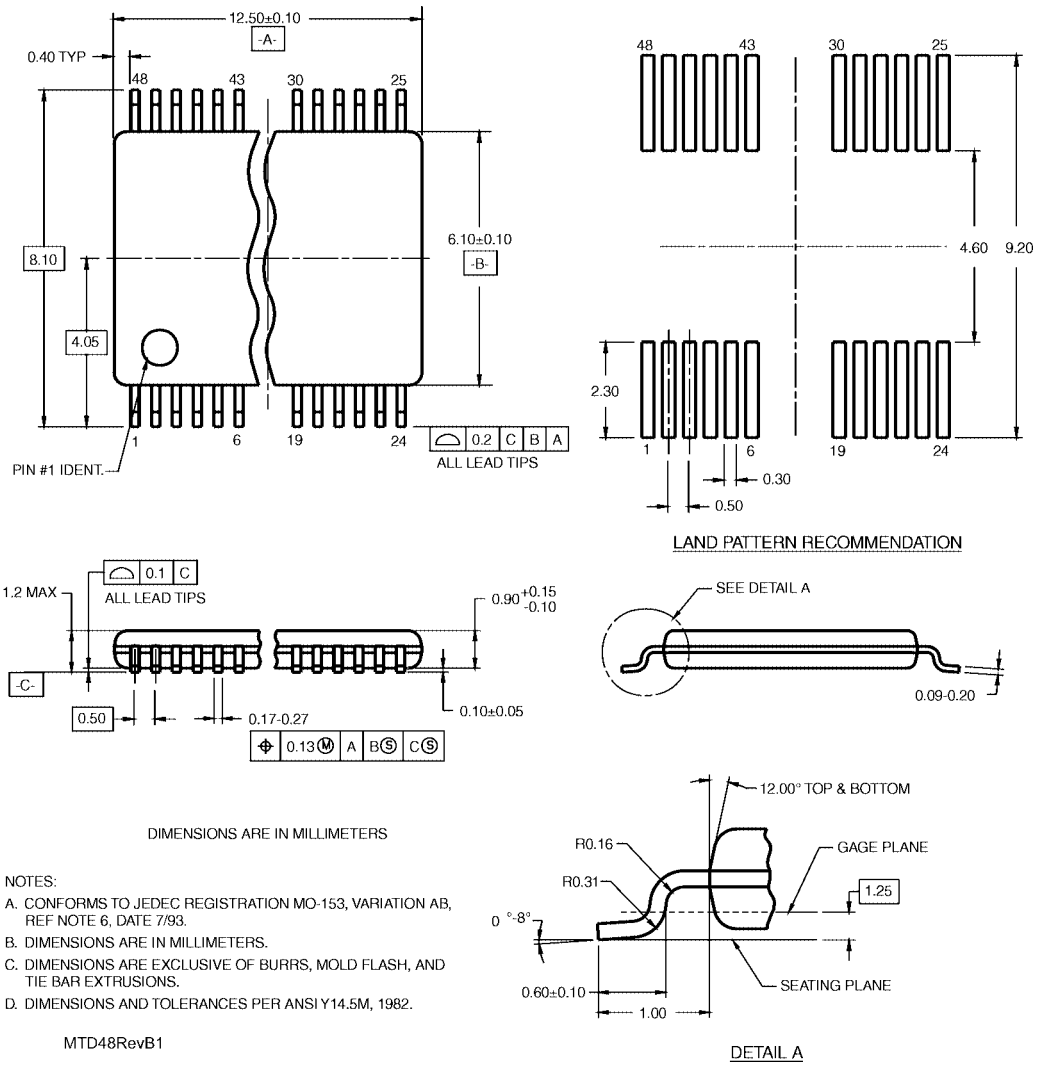
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1991
Revised November 1999

74ACTQ16374
16-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACTQ16374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and Output Enable (OE) are common to each byte and can be shorted together for full 16-bit operation.

The ACTQ16245 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

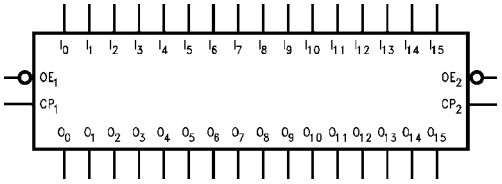
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Buffered Positive edge-triggered clock
- Separate control logic for each byte
- 16-bit version of the ACTQ374
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loadings specs for both 50 pF and 250 pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ16374SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

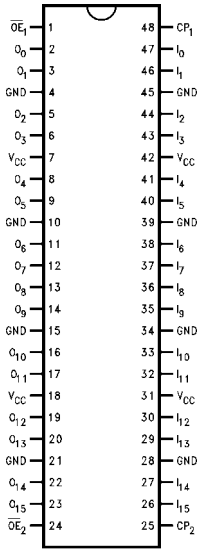
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



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Functional Description

The ACTQ16374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each byte has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operation of the OE_n input does not affect the state of the flip-flops.

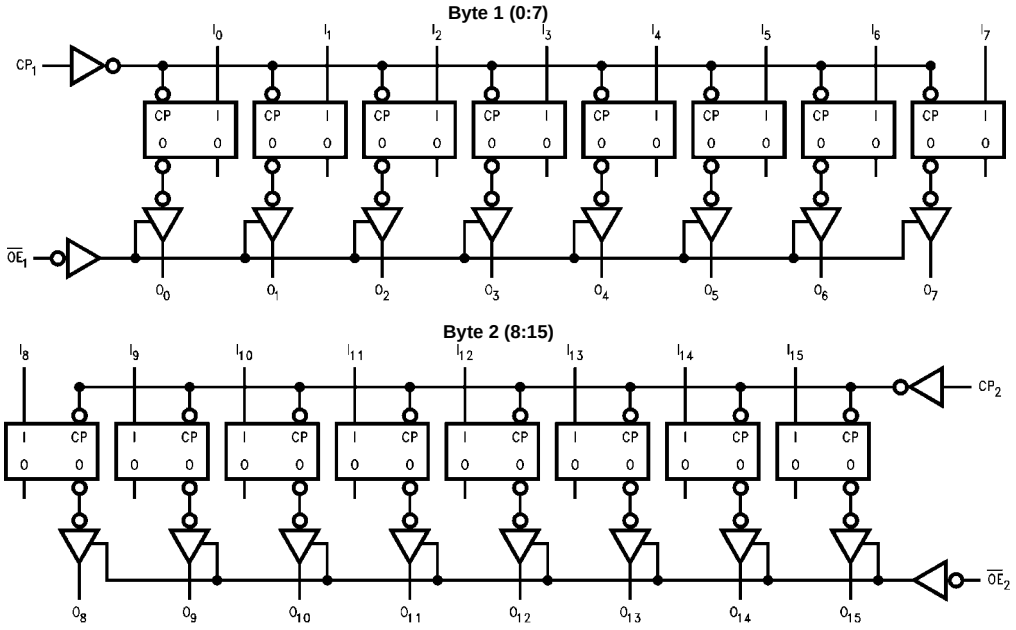
Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
⌐	L	H	H
⌐	L	L	L
L	L	X	(Previous)
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
⌐	L	H	H
⌐	L	L	L
L	L	X	(Previous)
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X= Immaterial
Z = HIGH Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagrams



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin	± 50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−1.0		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Maximum number of data inputs (n) switching. (n − 1) input switching 0V to 3V (ACTQ). Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	71			67		MHz
t_{PLH}	Propagation Delay	5.0	3.1	5.3	7.9	3.1	8.4	ns
t_{PHL}	CP to O_n		3.0	5.1	7.3	3.0	7.8	
t_{PZH}	Output Enable Time	5.0	2.5	4.7	7.4	2.5	7.9	ns
t_{PZL}			3.0	5.4	8.0	2.0	8.5	
t_{PHZ}	Output Disable Time	5.0	2.1	5.1	7.9	2.1	8.2	ns
t_{PLZ}			2.0	4.8	7.4	2.0	7.9	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Limits		
t_S	Setup Time, HIGH or LOW Input to Clock	5.0	0.7	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW Input to Clock	5.0	0.8	1.0	1.0	ns
t_W	CP Pulse Width, HIGH or LOW	5.0	1.5	5.0	5.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, 16 Outputs Switching (Note 10)			$T_A = -40°C$ to $+85°C$, $C_L = 250$ pF (Note 11)		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.7		13.3	6.6	16.3	ns
t_{PHL}	Data to Output	4.6		11.4	6.4	15.5	
t_{PZH}	Output Enable Time	3.5		10.4	(Note 13)		ns
t_{PZL}		3.8		10.9			
t_{PHZ}	Output Disable Time	3.4		8.5	(Note 14)		ns
t_{PLZ}		3.1		8.1			
t_{OSHL} (Note 12)	Pin to Pin Skew HL Data to Output			1.3			ns
t_{OSLH} (Note 12)	Pin to Pin Skew LH Data to Output			2.1			ns
t_{OST} (Note 12)	Pin to Pin Skew LH/HL Data to Output			4.0			ns

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Note 13: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 14: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

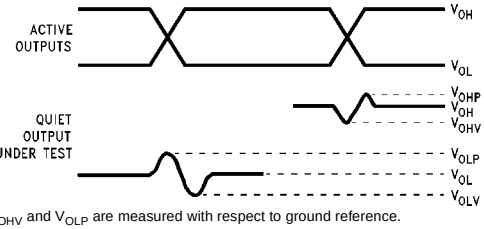
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or step out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level on the, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

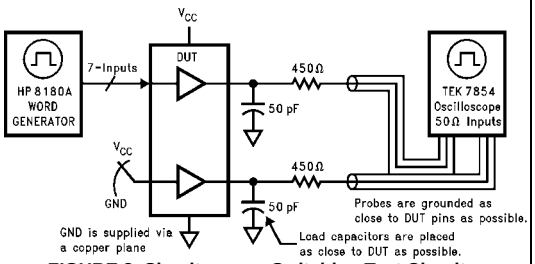
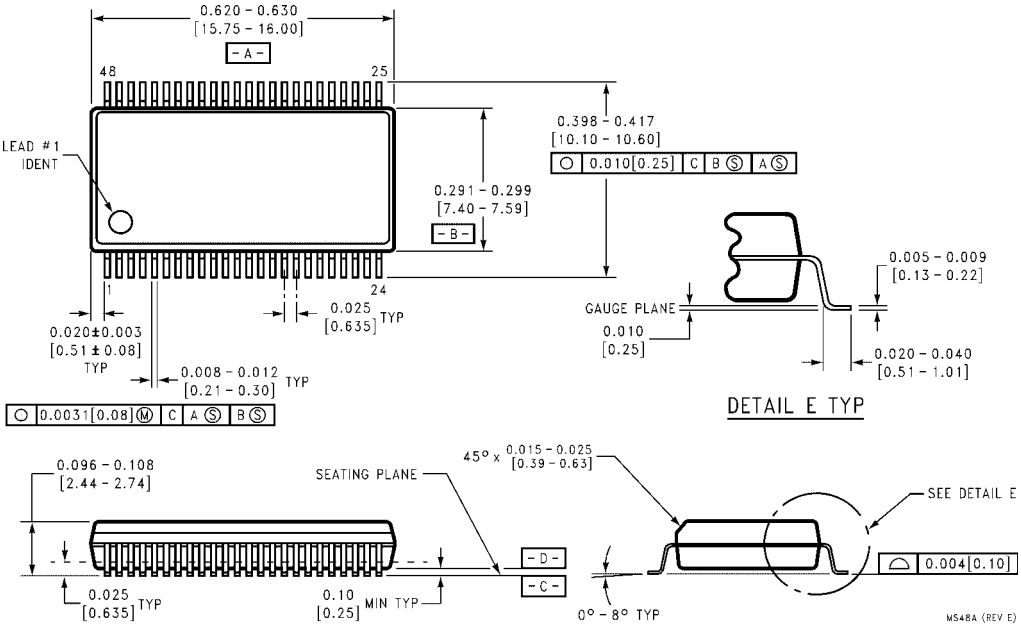


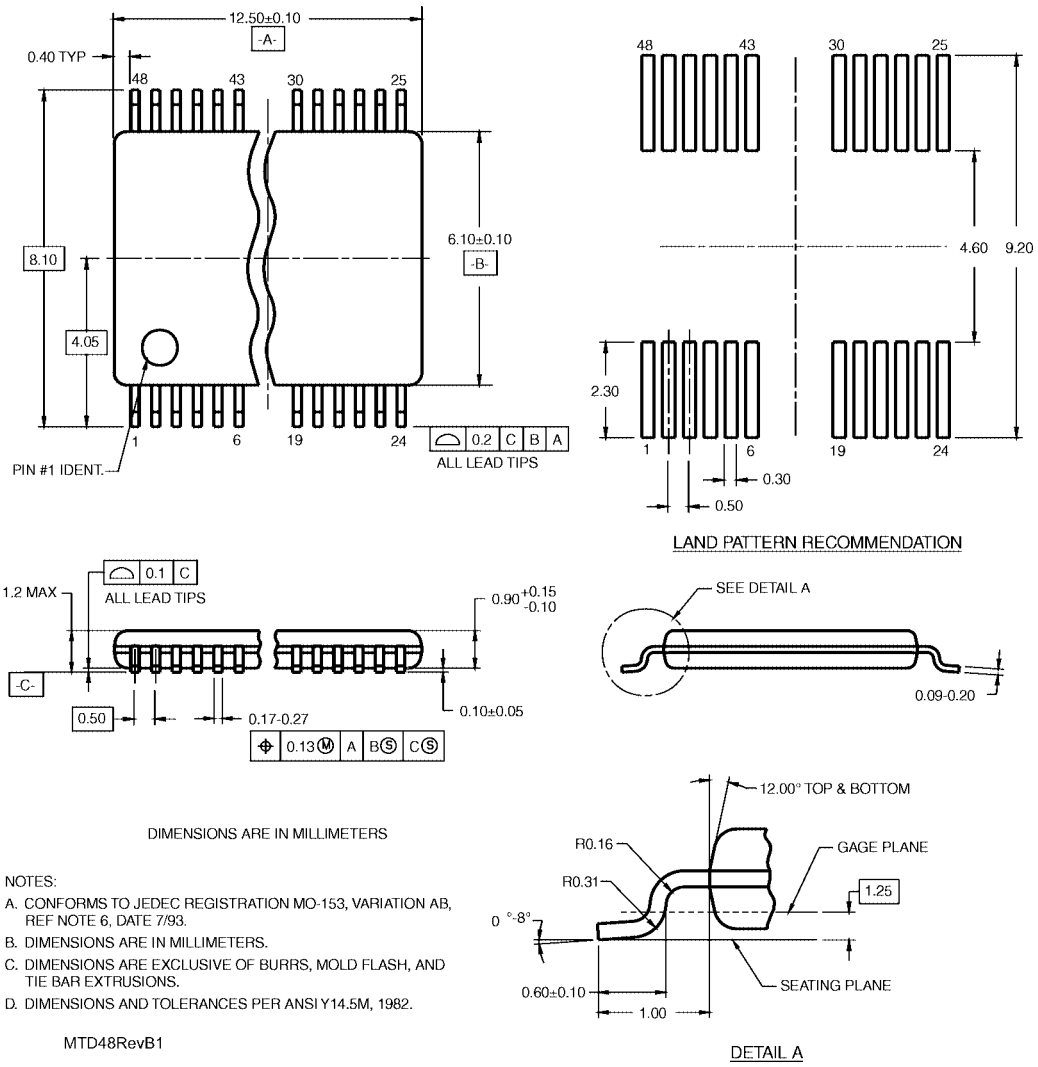
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1991
Revised November 1999

74ACTQ16540
16-Bit Inverting Buffer/Line Driver with 3-STATE Outputs

General Description

The ACTQ16540 contains sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The ACTQ16540 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

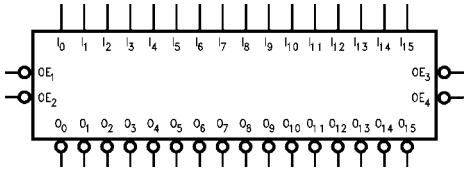
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte
- Outputs source/sink 24 mA
- Additional specs for multiple output switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

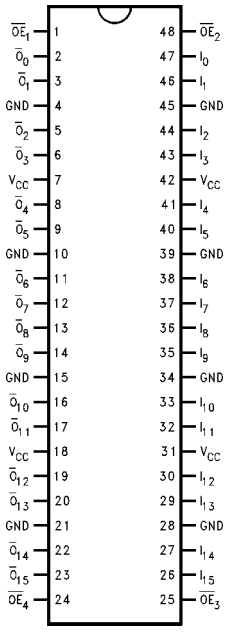
Order Number	Package Number	Package Description
74ACTQ16540SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16540MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

The ACTQ16540 contains sixteen inverting buffers with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

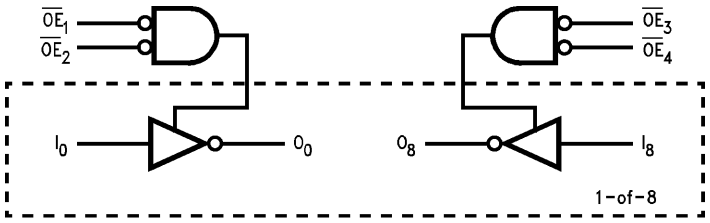
Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_7	$\overline{O}_0$–$\overline{O}_7$
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

Inputs			Outputs
$\overline{OE}_3$	$\overline{OE}_4$	I_8–I_{15}	$\overline{O}_8$–$\overline{O}_{15}$
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin	± 50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	µA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	µA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−1.0		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Maximum number of data inputs (n) switching. (n − 1) input switching 0V to 3V (ACTQ). Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Typ	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.7	4.9	7.3	2.7	7.8	ns
t_{PHL}	Data to Output		3.0	5.1	7.3	3.0	7.8	
t_{PZH}	Output Enable	5.0	2.5	4.8	7.4	2.5	7.9	ns
t_{PZL}	Time		2.7	5.3	8.0	2.7	8.5	
t_{PHZ}	Output Disable	5.0	2.5	5.4	8.3	2.5	8.7	ns
t_{PLZ}	Time		2.3	5.0	7.4	2.3	7.9	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, 16 Outputs Switching (Note 10)			$T_A = -40°C$ to $+85°C$, $C_L = 250$ pF (Note 11)		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay,	5.0	4.0		12.6	5.6	15.5	ns
t_{PHL}	Data to Output		4.0		10.0	5.6	13.6	
t_{PZH}	Output Enable Time	5.0	3.2		10.8	(Note 12)		ns
t_{PZL}			3.4		10.8			
t_{PHZ}	Output Disable Time	5.0	3.8		9.5	(Note 13)		ns
t_{PLZ}			3.1		9.2			
t_{OSHL} (Note 14)	Pin to Pin Skew, HL Data to Output	5.0			1.2			ns
t_{OSLH} (Note 14)	Pin to Pin Skew, LH Data to Output	5.0			2.5			ns
t_{OST} (Note 14)	Pin to Pin Skew, LH/HL Data to Output	5.0			4.3			ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 13: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

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Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
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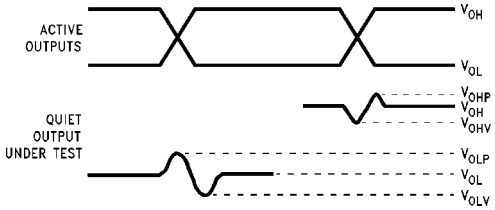
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the word generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

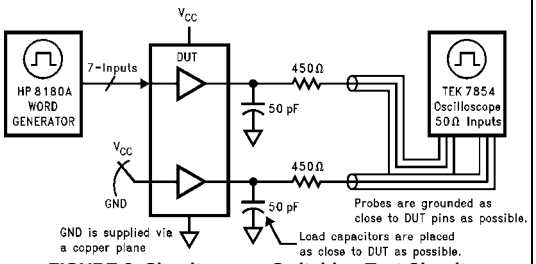
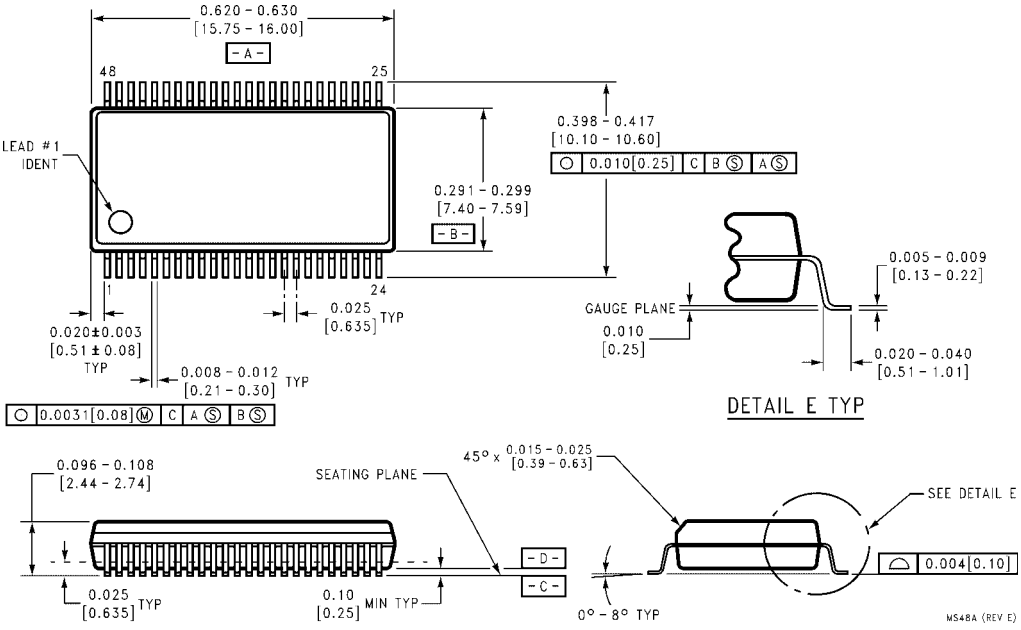


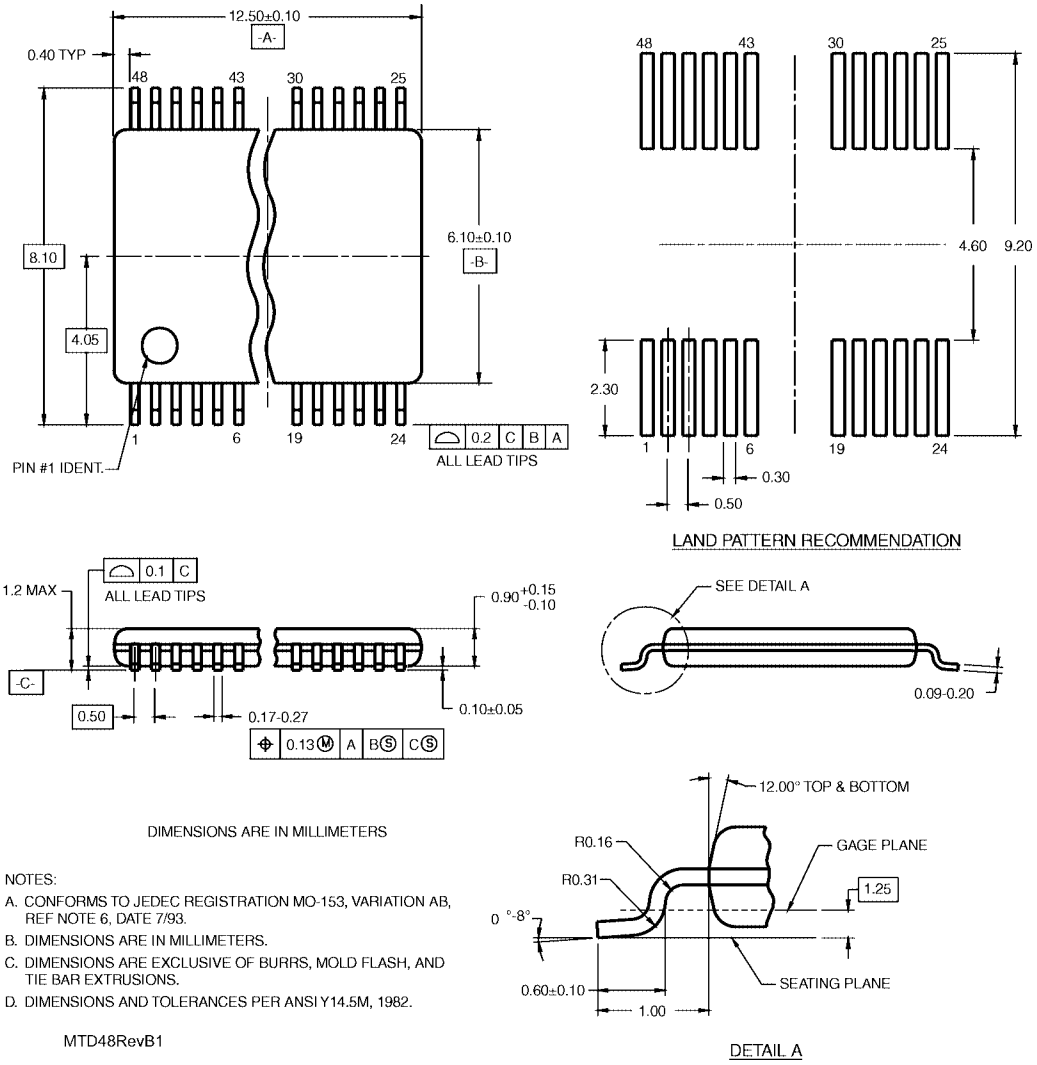
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1991
Revised November 1999

74ACTQ16541
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACTQ16541 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The ACTQ16541 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control for superior performance.

Features

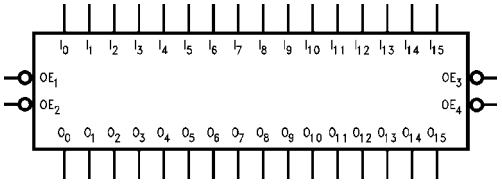
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte
- 16-bit version of the ACTQ541
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

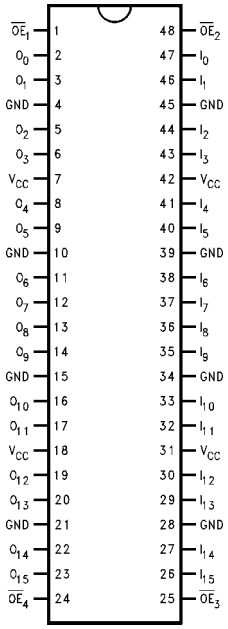
Order Number	Package Number	Package Description
74ACTQ16541SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16541MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

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Functional Description

The ACTQ16541 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

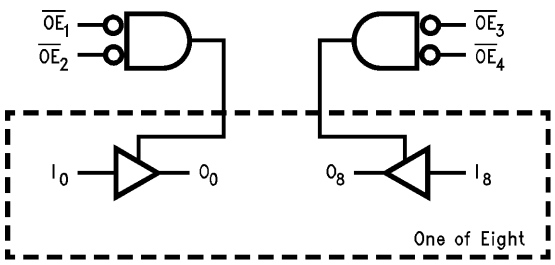
Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_7	O_0–O_7
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

Inputs			Outputs
$\overline{OE}_3$	$\overline{OE}_4$	I_8–I_{15}	O_8–O_{15}
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}					−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−1.0		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 7: Maximum number of data inputs (n) switching. (n − 1) input switching 0V to 3V. Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	3.0	5.2	7.3	3.0	7.8	ns
t_{PHL}	Data to Output		2.5	4.8	7.3	2.5	7.8	
t_{PZH}	Output Enable Time	5.0	2.6	5.0	7.4	2.6	7.9	ns
t_{PZL}			2.7	5.4	8.0	2.7	8.5	
t_{PHZ}	Output Disable Time	5.0	2.7	5.6	8.3	2.7	8.7	ns
t_{PLZ}			2.4	5.2	7.9	2.4	8.4	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, 16 Outputs Switching (Note 11)			$T_A = -40°C$ to $+85°C$, $C_L = 250$ pF (Note 12)		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay,	5.0	4.0		11.6	5.6	14.3	ns
t_{PHL}	Data to Output		3.4		9.6	4.8	13.1	
t_{PZH}	Output Enable Time	5.0	3.3		10.1	(Note 13)		ns
t_{PZL}			3.3		10.0			
t_{PHZ}	Output Disable Time	5.0	4.3		10.1	(Note 14)		ns
t_{PLZ}			3.8		9.6			
t_{OSHL} (Note 10)	Pin to Pin Skew, HL Data to Output	5.0			1.2			ns
t_{OSLH} (Note 10)	Pin to Pin Skew, LH Data to Output	5.0			2.5			ns
t_{OST} (Note 10)	Pin to Pin Skew, LH/HL Data to Output	5.0			4.3			ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Note 11: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 13: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 14: The Output Disable Time is dominated by the RC Network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

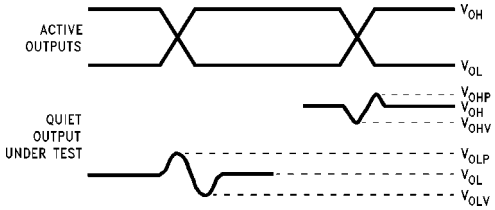
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note A: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note B: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV}on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case for active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

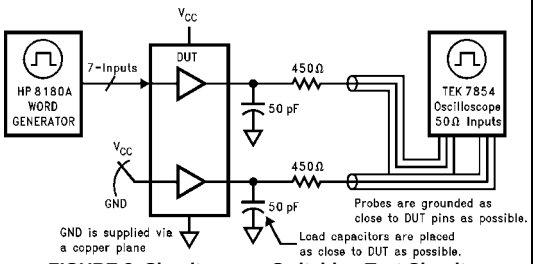
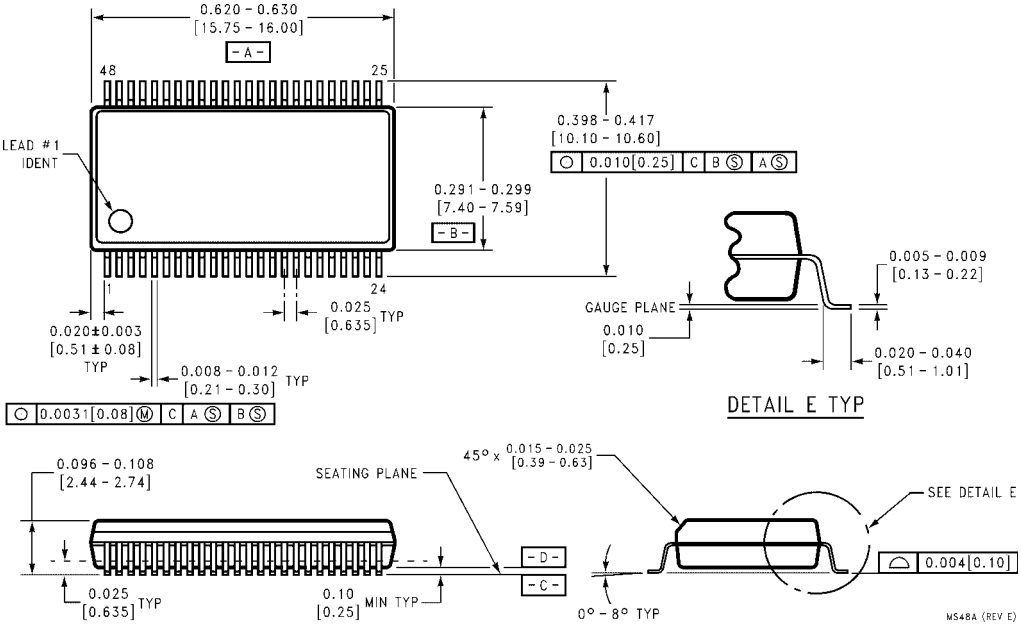


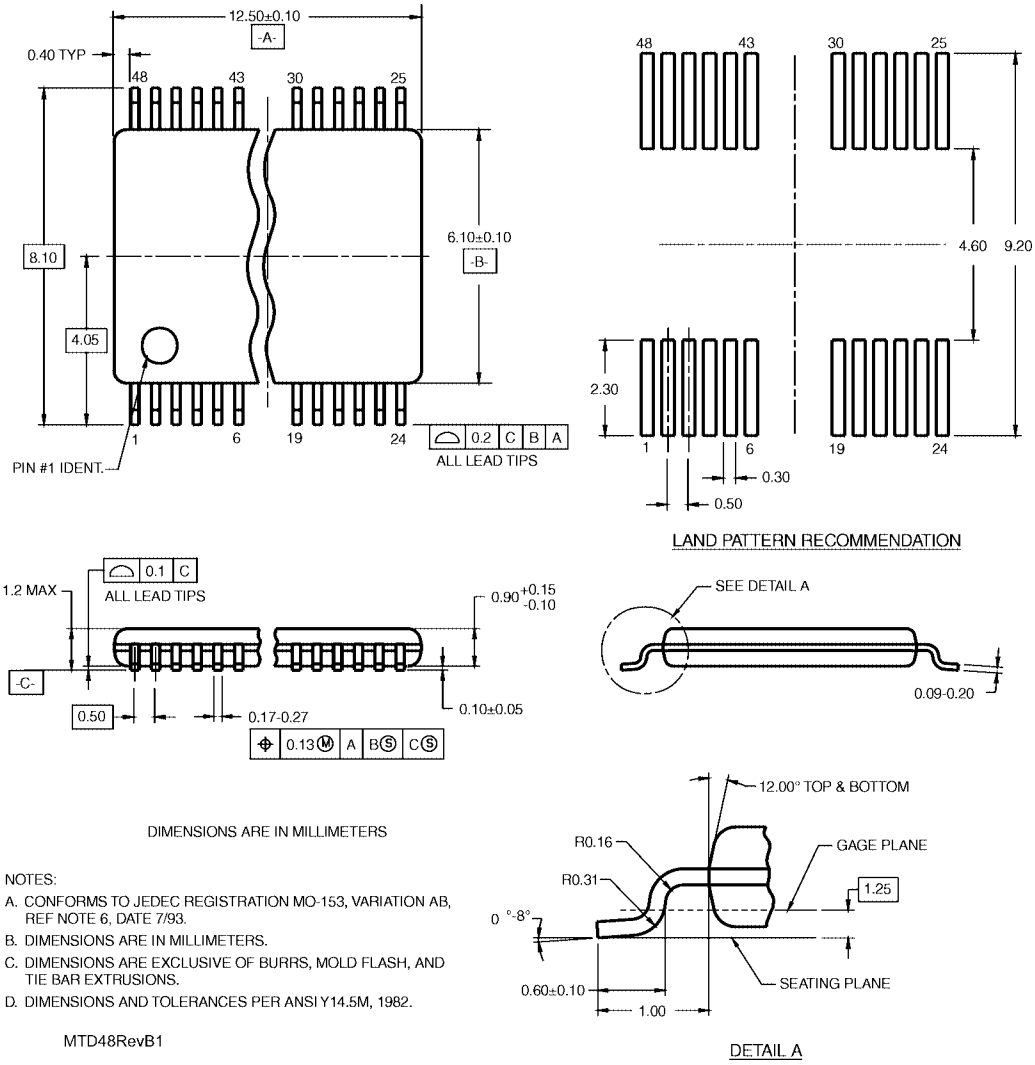
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

December 1991
Revised December 1998

74ACTQ16543
16-Bit Registered Transceiver with 3-STATE Outputs

General Description

The ACTQ16543 contains sixteen non-inverting transceivers containing two sets of D-type registers for temporary storage of data flowing in either direction. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The ACTQ16543 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector for superior performance.

Features

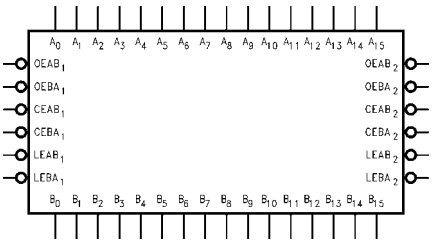
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Independent registers for A and B buses
- Separate controls for data flow in each direction
- Back-to-back registers for storage
  Multiplexed real-time and stored data transfers
- Separate control logic for each byte
- 16-bit version of the ACTQ543
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loading specs for both 50 pF and 250pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ16543SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16543MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

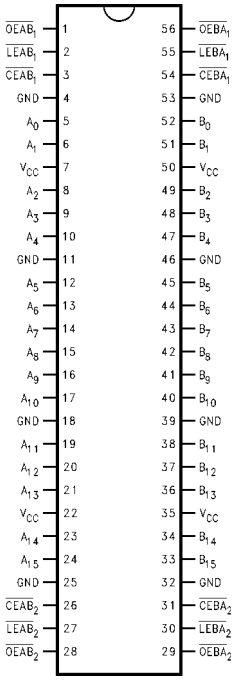


Pin Descriptions

Pin Names	Descriptions
$\overline{OEAB}_n$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}_n$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}_n$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}_n$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}_n$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}_n$	B-to-A Latch Enable Input (Active LOW)
A_0–A_{15}	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B_0–B_{15}	B-to-A Data Inputs or A-to-B 3-STATE Outputs

Connection Diagram

Pin Assignment for SSOP and TSSOP



Functional Description

The ACTQ16543 contains sixteen non-inverting transceivers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The following description applies to each byte. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}_n$) input must be LOW in order to enter data from A_0–A_{15} or take data from B_0–B_{15}, as indicated in the Data I/O Control Table. With $\overline{CEAB}_n$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}_n$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}_n$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}_n$ and $\overline{OEAB}_n$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$ inputs.

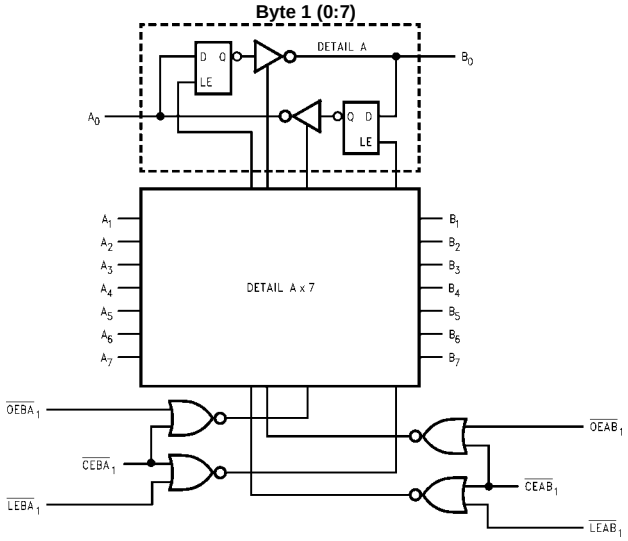
Data I/O Control Table

Inputs			Latch Status (Byte n)	Output Buffers (Byte n)
$\overline{CEAB}_n$	$\overline{LEAB}_n$	$\overline{OEAB}_n$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$

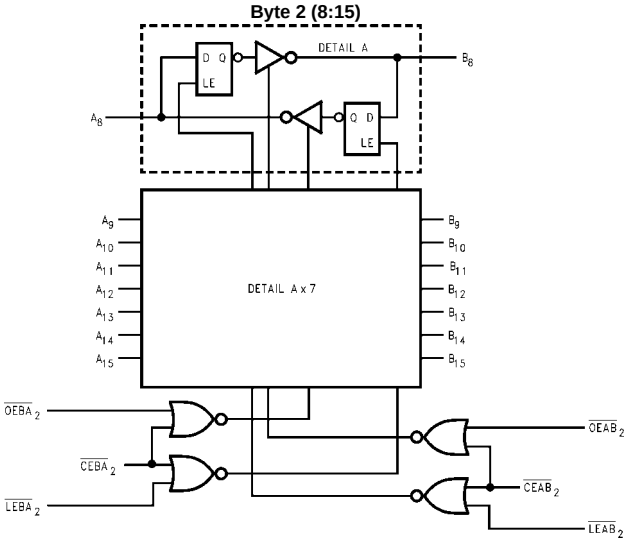
Logic Diagrams

Byte 1 (0:7)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZT}	Maximum I/O	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{IN}	Maximum Input	5.5		±0.1	±1.0	μA	V_I = V_{CC},
	Leakage Current						GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent	5.5		8.0	80.0	μA	V_{IN} = V_{CC}
	Supply Current						or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output	5.0	0.5	0.8		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)
V_{OLV}	Quiet Output	5.0	−0.5	−0.8		V	Figure 1, Figure 2
	Minimum Dynamic V_{OL}						(Note 5)(Note 6)
V_{OHP}	Maximum	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2
	Overshoot						(Note 4)(Note 6)
V_{OHV}	Minimum	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2
	V_{CC} Droop						(Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic	5.0	1.7	2.0		V	(Note 4)(Note 7)
	Input Voltage Level						
V_{ILD}	Maximum LOW Dynamic	5.0	1.2	0.8		V	(Note 4)(Note 7)
	Input Voltage Level						

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

Note 4: Worst case package.

DC Electrical Characteristics (Continued)

Note 5: Maximum number of outputs that can switch simultaneously is n. (n – 1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n – 1) outputs are switched HIGH and one output held HIGH.

Note 7: Maximum number of data inputs (n) switching. (n – 1) inputs switching 0V to 3V Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay		3.8	5.9	8.3	3.0	9.0	
t_{PHL}	Transparent Mode	5.0	3.5	5.5	7.9	2.6	8.5	ns
	A_n to $B_n$or B_n to A_n							
t_{PLH}	Propagation Delay		4.7	6.9	9.8	3.4	10.8	
t_{PHL}	$\overline{LEBA}_n$, $\overline{LEAB}_n$	5.0	3.9	6.3	9.0	3.1	9.8	ns
	to A_n, B_n							
t_{PZH}	Output Enable Time		4.2	6.3	9.2	3.0	9.9	
t_{PZL}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n	5.0	4.9	7.3	10.3	3.6	10.3	ns
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n							
t_{PHZ}	Output Disable Time		2.8	5.2	8.0	2.1	8.3	
t_{PLZ}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n	5.0	2.6	5.0	7.6	2.0	8.1	ns
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n							

Note 8: Voltage Range 5.0 is 5.0V ±0.5V.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	5.0		3.0	3.0	ns
	A_n or B_n to $\overline{LEBA}_n$ or $\overline{LEAB}_n$					
t_H	Hold Time, HIGH or LOW	5.0		1.5	1.5	ns
	A_n or B_n to $\overline{LEBA}_n$ or $\overline{LEAB}_n$					
t_W	Latch Enable, B to A	5.0		4.0	4.0	ns
	Pulse Width, LOW					

Note 9: Voltage Range 5.0 is 5.0V ±0.5V

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40$ to $+85°C$, V_{CC} = Com, C_L = 50 pF, 16 Outputs Switching (Note 10)			$T_A = -40$ to $+85°C$, V_{CC} = Com, C_L = 250 pF (Note 11)		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.5		11.1	5.8	14.3	
t_{PHL}	Transparent Mode	3.7		9.6	5.1	13.4	ns
	A_n to B_n or B_n to A_n						
t_{PLH}	Propagation Delay	4.3		11.3	6.2	16.3	ns
t_{PHL}	$\overline{LEBA}_n$, $\overline{LEAB}_n$ to A_n, B_n	3.7		9.7	5.8	14.9	
t_{PZH}	Output Enable Time	4.0		10.7			
t_{PZL}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n	4.3		11.3	(Note 12)		ns
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n						
t_{PHZ}	Output Disable Time	3.0		8.0			
t_{PLZ}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n	2.8		7.6	(Note 13)		ns
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n						
t_{OSHL}	Pin to Pin Skew			1.1			ns
(Note 14)	HL Data to Output						
t_{OSLH}	Pin to Pin Skew			1.4			ns
(Note 14)	LH Data to Output						
t_{OSHL}	Pin to Pin Skew			2.6			ns
(Note 14)	Latch to Output						
t_{OSLH}	Pin to Pin Skew			1.0			ns
(Note 14)	Latch to Output						
t_{OST}	Pin to Pin Skew			1.0			ns
(Note 14)	Data to Output						
t_{OST}	Pin to Pin Skew			2.2			ns
(Note 14)	Latch to Output						

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all low-to-high, high-to-low, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 13: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}).

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation.Capacitance	95.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

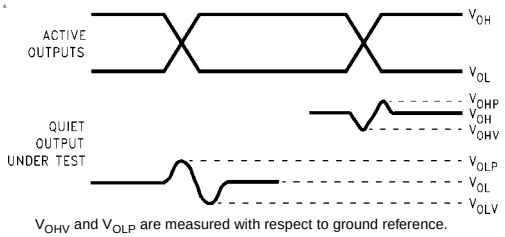
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
6. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV}on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case for active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability on the measurements.

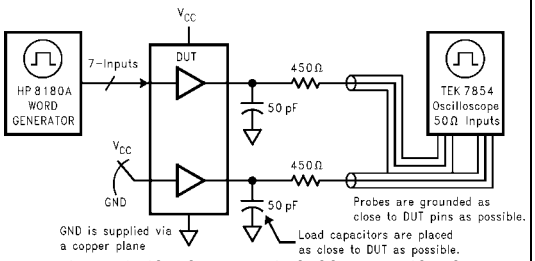
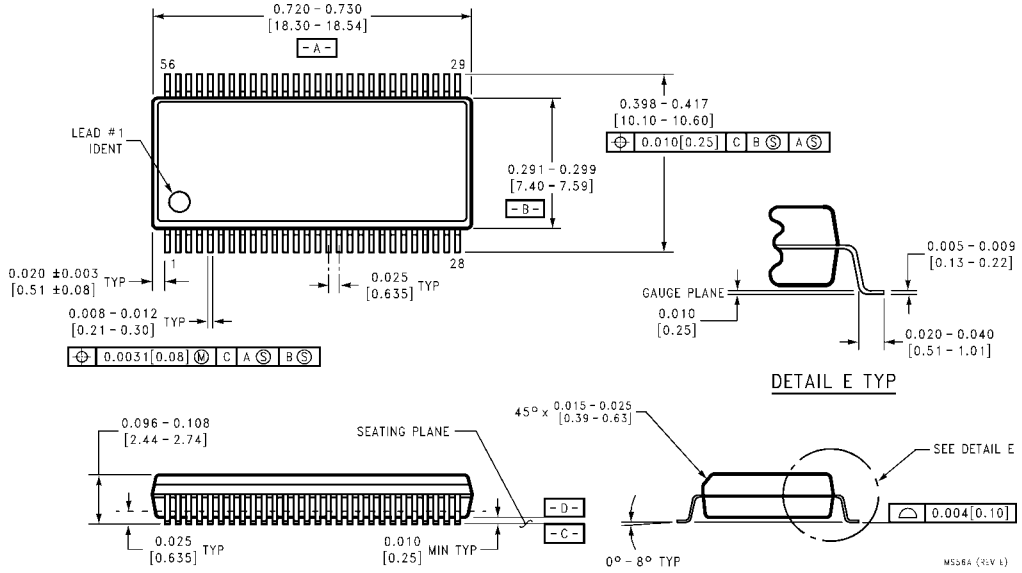


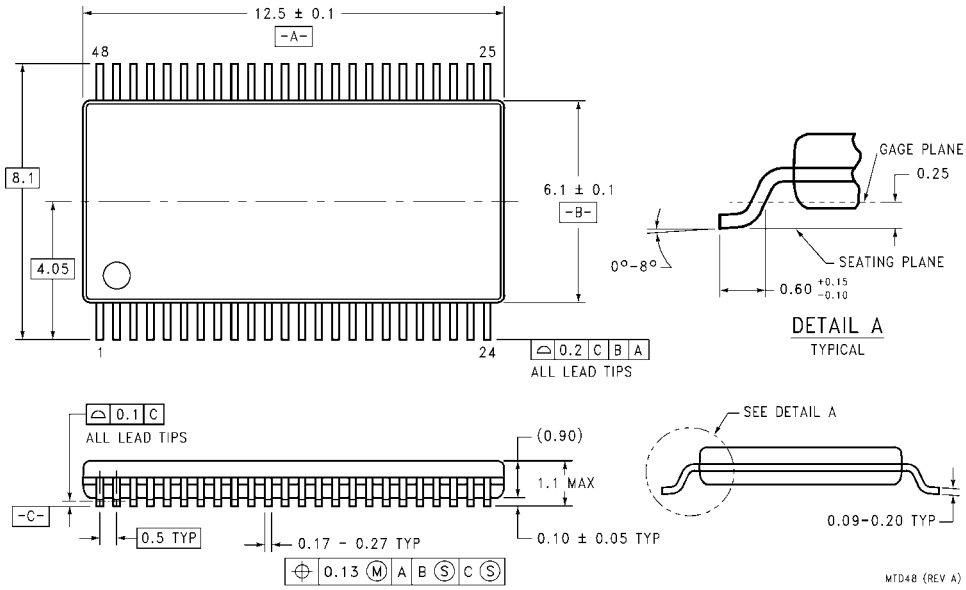
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (SSOP), JEDEC MO-153, 6.1mm Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1991
Revised January 1999

74ACTQ16646
16-Bit Transceiver/Register with 3-STATE Outputs

General Description

The ACTQ16646 contains sixteen non-inverting bidirectional registered bus transceivers providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition. The ACTQ16646 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector for superior performance.

Features

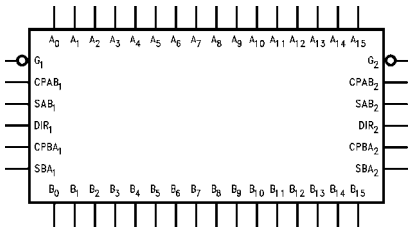
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Independent registers for A and B buses
- Multiplexed real-time and stored data transfers
- Separate control logic for each byte
- 16-bit version of the ACTQ646
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ16646SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16646MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

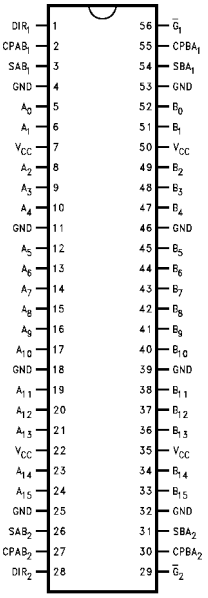
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram

Pin Assignment for SSOP and TSSOP



FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

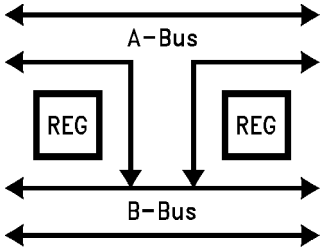
Function Table

Inputs						Data I/O (Note 1)		Output Operation Mode
G_1	DIR_1	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_{0-7}	B_{0-7}	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock An Data into A Register
H	X	X	↑	X	X			Clock Bn Data Into B Register
L	H	X	X	L	X			An to Bn—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock An Data to A Register
L	H	H or L	X	H	X			A Register to Bn (Stored Mode)
L	H	↑	X	H	X			Clock An Data into A Register and Output to Bn
L	L	X	X	X	L			Bn to An—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock Bn Data into B Register
L	L	X	H or L	X	H			B Register to An (Stored Mode)
L	L	X	↑	X	H			Clock Bn into B Register and Output to An

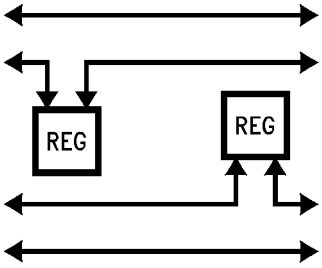
H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level ↑ = LOW-to-HIGH Transition.

Note 1: The data output functions may be enabled or disabled by various signals at the G and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

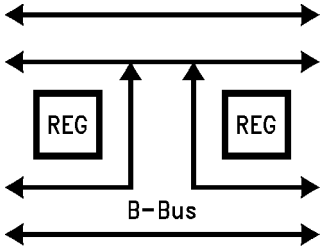
Real Time Transfer A-Bus to B-Bus



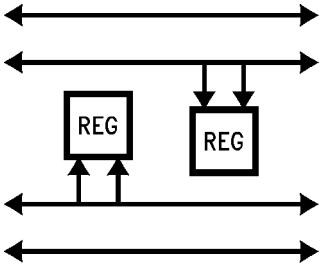
Storage from Bus to Register



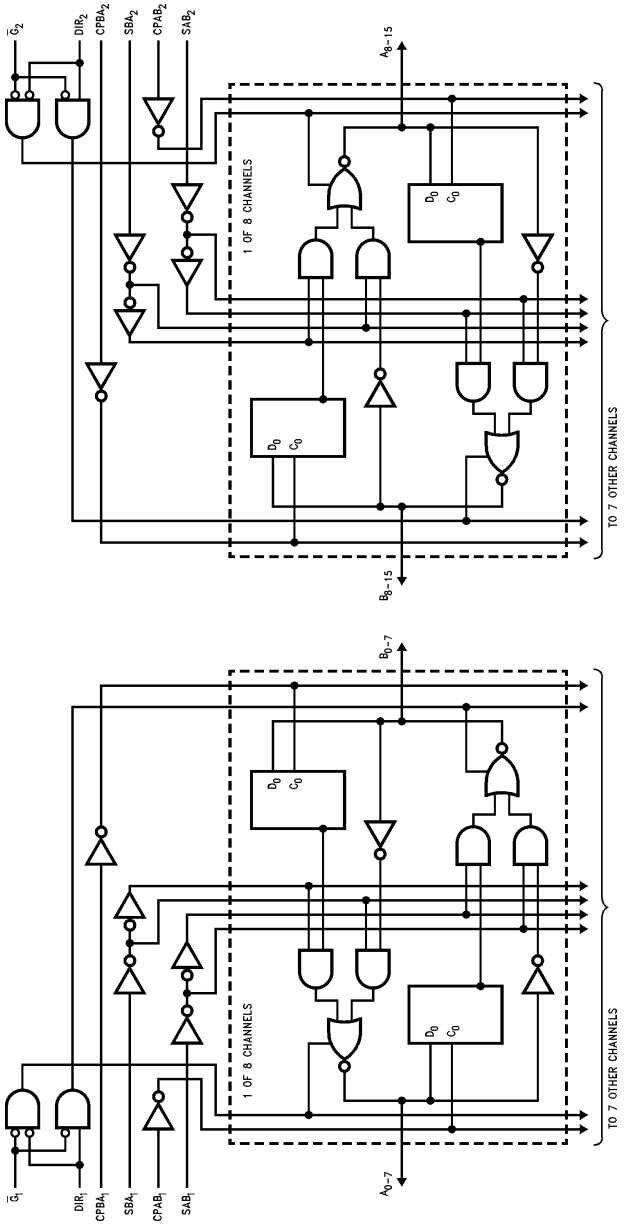
Real Time Transfer B-Bus to A-Bus



Transfer from Register to Bus



Logic Diagram



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{OZT}	Maximum I/O	5.5		±0.5	±5.0	μA	V_{IN} = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{IN}	Maximum Input	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
	Leakage Current						
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{CC}	Max Quiescent	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
	Supply Current						
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quick Output	5.0	0.5	0.8		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 6)(Note 7)
V_{OLV}	Quick Output	5.0	−0.5	−0.8		V	Figure 1, Figure 2
	Minimum Dynamic V_{OL}						(Note 6)(Note 7)
V_{OHP}	Maximum	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2
	Overshoot						(Note 5)(Note 7)
V_{OHV}	Minimum	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2
	V_{CC} Droop						(Note 5)(Note 7)
V_{IHD}	Minimum HIGH Dynamic	5.0	1.7	2.0		V	(Note 5)(Note 8)
	Input Voltage Level						
V_{ILD}	Maximum LOW Dynamic	5.0	1.2	0.8		V	(Note 5)(Note 8)
	Input Voltage Level						

Note 3: All outputs loaded; thresholds associated with output under test.

Note 4: Maximum test duration 2.0 ms; one output loaded at a time.

Note 5: Worst case package.

DC Electrical Characteristics (Continued)

Note 6: Maximum number of outputs that can switch simultaneously is n. (n – 1) outputs are switched LOW and one output held LOW.

Note 7: Maximum number of outputs that can switch simultaneously is n. (n – 1) outputs are switched HIGH and one output held HIGH.

Note 8: Maximum number of data inputs (n) switching. (n – 1) inputs switching 0V to 3V (ACTQ). Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	4.6	6.9	9.4	3.6	10.1	ns
t_{PLH}	Clock to Bus		4.3	6.5	8.9	3.3	9.7	
t_{PHL}	Propagation Delay	5.0	4.0	6.2	8.5	2.9	9.2	ns
t_{PLH}	Bus to Bus		4.1	6.4	8.6	3.2	9.3	
t_{PHL}	Propagation Delay	5.0	4.0	6.4	8.9	3.1	9.6	ns
t_{PLH}	Select to Bus		4.2	6.7	9.5	3.2	10.4	
	(w/An or Bn HIGH or LOW)							
t_{PZL}	Enable Time	5.0	5.3	7.8	10.5	3.8	11.4	ns
t_{PZH}	G to An/Bn		4.6	6.9	9.4	3.3	10.2	
t_{PLZ}	Disable Time	5.0	3.0	5.5	8.1	2.3	8.6	ns
t_{PHZ}	G to An/Bn		3.4	5.7	8.3	2.6	8.6	
t_{PZL}	Enable Time	5.0	5.1	8.2	11.8	4.3	12.7	ns
t_{PZH}	DIR to An/Bn		4.6	7.5	10.8	3.7	11.7	
t_{PLZ}	Disable Time	5.0	2.9	5.8	9.2	2.0	9.8	ns
t_{PHZ}	DIR to An/Bn		3.4	6.1	9.2	2.5	9.7	

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Guaranteed Minimum		
t_S	Setup Time, H or L Bus to Clock	5.0	3.0	3.0	ns
t_H	Hold Time, H or L Bus to Clock	5.0	1.5	1.5	ns
t_W	Clock Pulse Width H or L	5.0	4.0	4.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, V_{CC} = Com, C_L = 50 pF, 16 Outputs Switching (Note 12)			$T_A = -40°C$ to $+85°C$, V_{CC} = Com, C_L = 250 pF (Note 13)		Units
		Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	4.1		10.1	6.1	14.5	ns
t_{PLH}	Clock to Bus	4.2		10.1	6.0	14.8	
t_{PHL}	Propagation Delay	4.0		10.0	5.4	13.7	ns
t_{PLH}	Bus to Bus	4.7		10.7	5.9	13.5	
t_{PHL}	Propagation Delay	3.8		9.6	5.7	14.2	ns
t_{PLH}	Select to Bus (w/An or Bn HIGH or LOW)	4.3		10.9	6.1	15.5	
t_{PZL}	Enable Time	5.0		12.7	(Note 14)		ns
t_{PZH}	G to An/Bn	4.1		11.3			
t_{PLZ}	Disable Time	3.2		8.3	(Note 15)		ns
t_{PHZ}	G to An/Bn	3.5		8.6			
t_{PZL}	Enable Time	4.1		11.3	(Note 14)		ns
t_{PZH}	DIR to An/Bn	4.4		13.0			
t_{PLZ}	Disable Time	2.9		9.5	(Note 15)		ns
t_{PHZ}	DIR to An/Bn	3.4		9.7			
t_{OSHL} (Note 11)	Pin-to-Pin Skew Clock to Bus			1.0			ns
t_{OSLH} (Note 11)	Pin-to-Pin Skew Clock to Bus			1.0			ns
t_{OSHL} (Note 11)	Pin-to-Pin Skew Bus to Bus			1.0			ns
t_{OSLH} (Note 11)	Pin-to-Pin Skew Bus to Bus			1.0			ns
t_{OSHL} (Note 11)	Pin-to-Pin Skew Select to Bus (w/An or Bn HIGH or LOW)			1.0			ns
t_{OSLH} (Note 11)	Pin-to-Pin Skew Select to Bus (w/An or Bn HIGH or LOW)			1.2			ns
t_{OST} (Note 11)	Pin-to-Pin Skew Clock to Bus			2.1			ns
t_{OST} (Note 11)	Pin-to-Pin Skew Bus to Bus			1.0			ns
t_{OST} (Note 11)	Pin-to-Pin Skew Select to Bus			2.7			ns

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}).

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 13: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 14: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 15: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	95	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

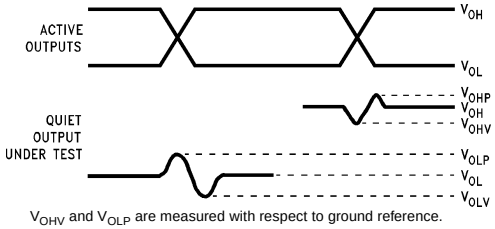
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the word generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

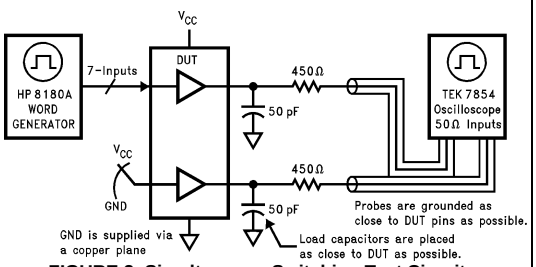
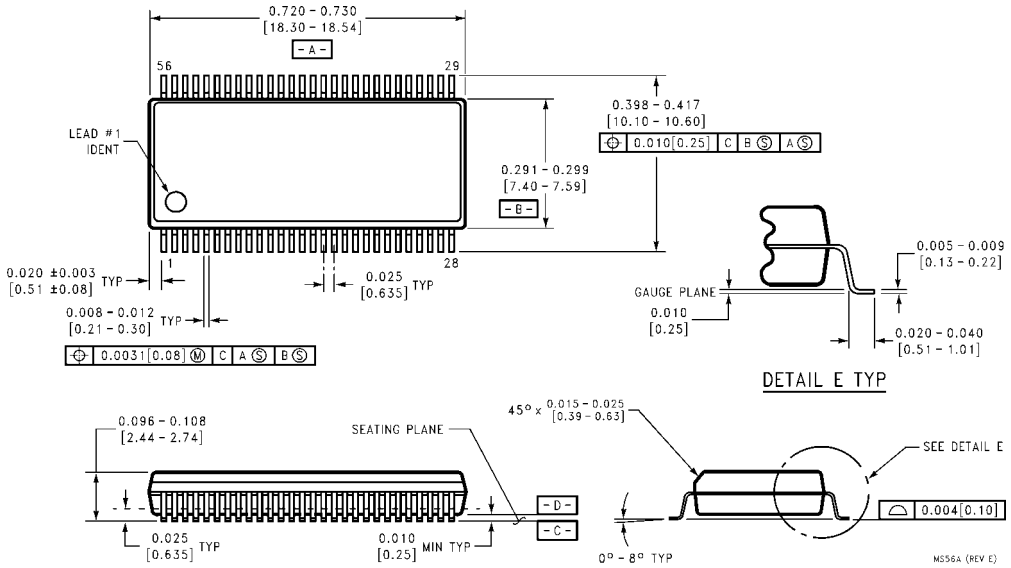


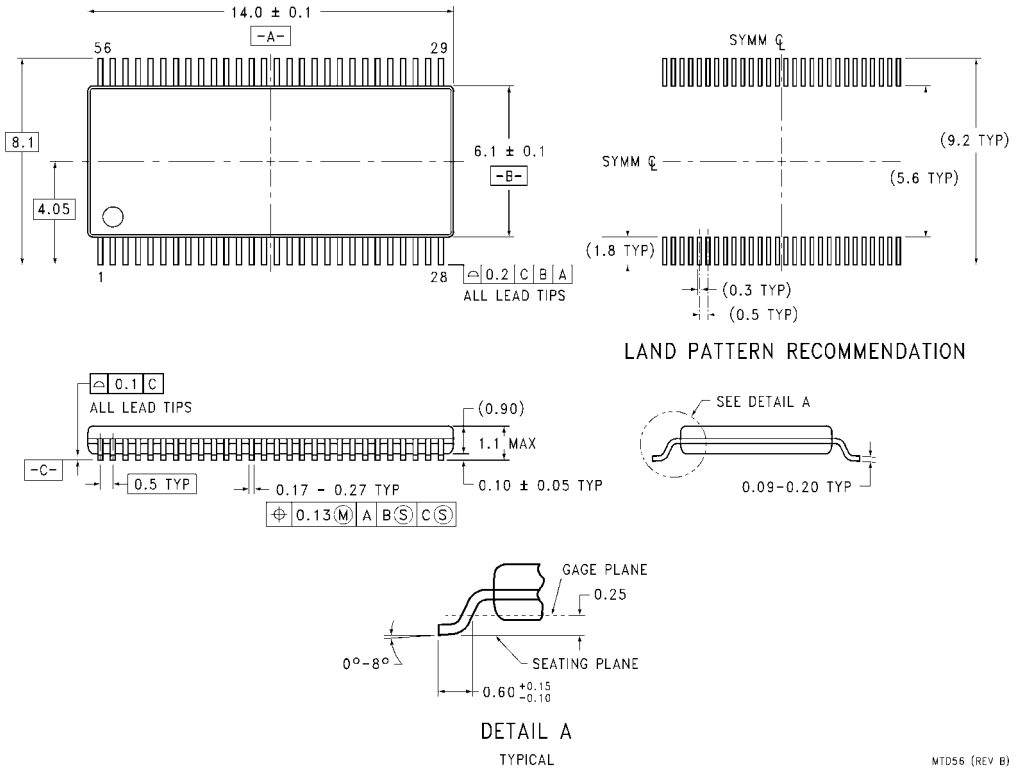
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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September 1991
Revised November 1999

74ACTQ18823
18-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACTQ18823 contains eighteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP), Clear ($\overline{CLR}$), Clock Enable ($\overline{EN}$) and Output Enable ($\overline{OE}$) are common to each byte and can be shorted together for full 18-bit operation.

The ACTQ18823 utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector for superior performance.

Features

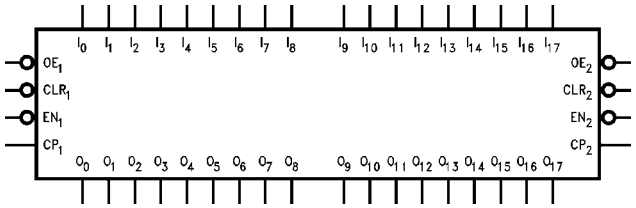
- Utilizes Fairchild's FACT Quiet Series technology
- Broadside pinout allows for easy board layout
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte
- Extra data width for wider address/data paths or buses carrying parity
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ18823SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ18823MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

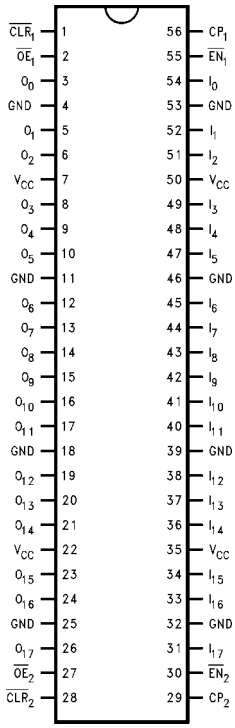


Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$\overline{CLR}_n$	Clear (Active LOW)
$\overline{EN}_n$	Clock Enable (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{17}	Inputs
O_0–O_{17}	Outputs

FACT™, Quiet Series™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Connection Diagram



Functional Description

The ACTQ18823 consists of eighteen D-type edge-triggered flip-flops. These have 3-STATE outputs for bus systems organized with inputs and outputs on opposite sides. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. The buffered clock (CP_n) and buffered Output Enable ($\overline{OE}_n$) are common to all flip-flops within that byte. The flip-flops will store the state of their individual D inputs that meet set-up and hold time requirements on the LOW-to-HIGH CP_n transition. With $\overline{OE}_n$ LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the impedance state. Operation of the $\overline{OE}_n$ input does not affect the state of the flip-flops. In addition to the Clock and Output Enable pins, there are Clear ($\overline{CLR}_n$) and Clock Enable ($\overline{EN}_n$) pins. These devices are ideal for parity bus interfacing in high performance systems.

When $\overline{CLR}_n$ is LOW and $\overline{OE}_n$ is LOW, the outputs are LOW. When $\overline{CLR}_n$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}_n$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}_n$ is HIGH, the outputs do not change state, regardless of the data or clock input transitions.

Function Table (Note 1)

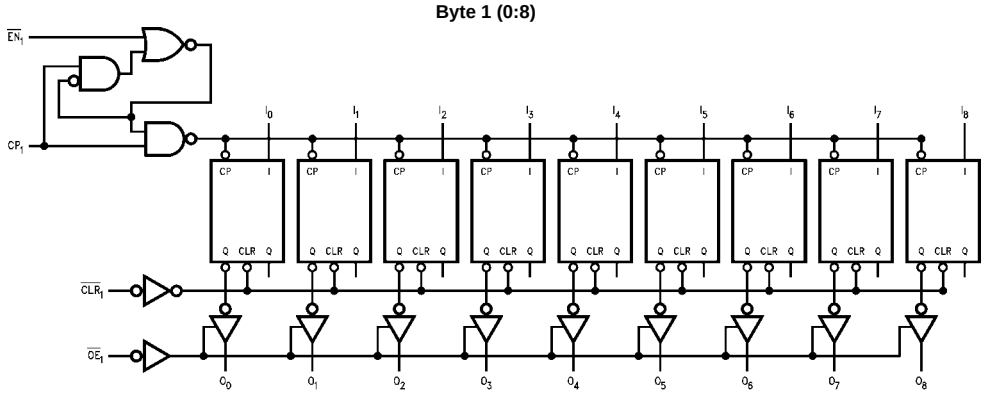
Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	I_n	Q	O_n	
H	X	L	⌐	L	L	Z	High Z
H	X	L	⌐	H	H	Z	High Z
H	L	X	X	X	L	Z	Clear
L	L	X	X	X	L	L	Clear
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	H	L	⌐	L	L	Z	Load
H	H	L	⌐	H	H	Z	Load
L	H	L	⌐	L	L	L	Load
L	H	L	⌐	H	H	H	Load

H= HIGH Voltage Level
L= LOW Voltage Level
X= Immaterial
Z= High Impedance
⌐= LOW-to-HIGH Transition
NC= No Change

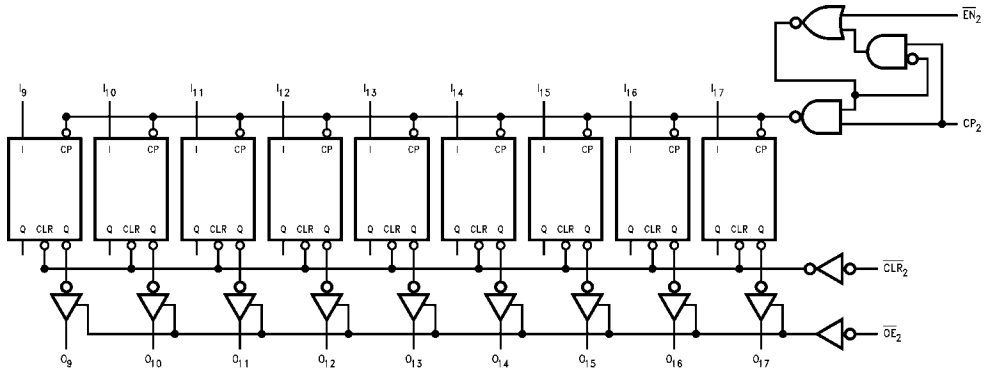
Note 1: The table represents the logic for one byte. The two bytes are independent of each other and function identically.

Logic Diagrams

Byte 1 (0:8)



Byte 2 (9:17)



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
Per Output Pin	± 50 mA
Junction Temperature	
PDIP/SOIC	+140°C
Storage Temperature	−65°C to +150°C
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
		(V)	Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	(Note 6)(Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−0.8		V	(Note 6)(Note 7)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	(Note 5)(Note 7)
V_{OHV}	Minimum V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	(Note 5)(Note 7)
V_{IHD}	Minimum High Voltage Level	5.0	1.7	2.0		V	(Note 5)(Note 8)
V_{ILD}	Maximum Low Dynamic Input Voltage Level	5.0	1.2	1.2		V	(Note 5)(Note 8)

Note 3: All outputs loaded; thresholds associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Worst case package.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched LOW and one output held LOW.

Note 7: Maximum number of outputs that can switch simultaneously is n. (n − 1) outputs are switched HIGH and one output held HIGH.

Note 8: Maximum number of data inputs (n) switching. (n − 1) input switching 0V to 3V. Input under test switching 3V to threshold (V_{ILD}).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	100			90		MHz
t_{PHL}	Propagation Delay	5.0	2.0		9.0	2.0	9.5	ns
t_{PLH}	CP_n to O_n		2.0		9.0	2.0	9.5	
t_{PHL}	Propagation Delay $\overline{CLR}_n$ to O_n	5.0	2.0		9.0	2.0	9.5	ns
t_{PZL}	Output Enable Time	5.0	2.0		9.0	2.0	10.0	ns
t_{PZH}			2.0		9.0	2.0	10.0	
t_{PLZ}	Output Disable Time	5.0	1.5		7.0	1.5	7.5	ns
t_{PHZ}			1.5		8.0	1.5	8.5	

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW, Input to Clock	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW, Input to Clock	5.0		1.5	1.5	ns
t_S	Setup Time, HIGH or LOW, Enable to Clock	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW, Enable to Clock	5.0		1.5	1.5	ns
t_W	$\overline{CP}_n$ Pulse Width, HIGH or LOW	5.0		4.0	4.0	ns
t_W	$\overline{CLR}_n$ Pulse Width, HIGH or LOW	5.0		4.0	4.0	ns
t_{REC}	Recovery Time, $\overline{CLR}_n$ to CP_n	5.0		6.0	6.0	ns

Note 10: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, V_{CC} = Com, C_L = 50 pF, 16 Outputs Switching (Note 12)			$T_A = -40°C$ to $+85°C$, V_{CC} = Com, C_L = 250 pF (Note 13)		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.2	6.5	7.6	7.0	9.8	ns
t_{PHL}	CP_n to O_n	5.3	6.5	7.8	6.8	10.0	
t_{PHL}	Propagation Delay $\overline{CLR}_n$ to O_n	4.8	5.3	6.2	5.2	7.5	ns
t_{PZH}	Output Enable Time	4.2	4.8	6.5	(Note 14)		ns
t_{PZL}		4.4	5.3	6.0			
t_{PHZ}	Output Disable Time	3.5	4.2	4.8	(Note 15)		ns
t_{PZL}		4.6	5.2	6.0			
t_{OSHL} (Note 11)	Pin to Pin Skew CP_n to O_n			1.0			ns
t_{OSLH} (Note 11)	Pin to Pin Skew CP_n to O_n			1.0			ns
t_{OSHL} (Note 11)	Pin to Pin Skew $\overline{CLR}_n$ to Output			1.0			ns
t_{OST} (Note 11)	Pin to Pin Skew CP_n to Output			1.5			ns

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Note 12: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (il.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 13: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 14: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 15: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	V_{CC} = 5.0V
C_{PD}	Power Dissipation Capacitance	95	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

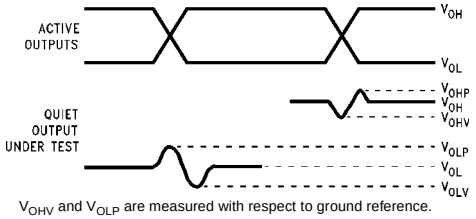
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillator steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

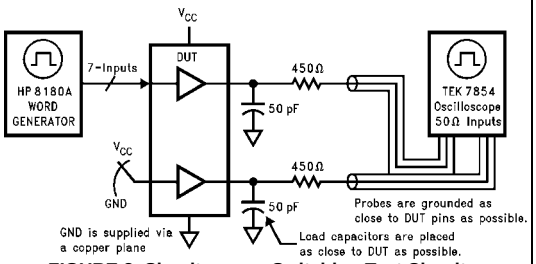
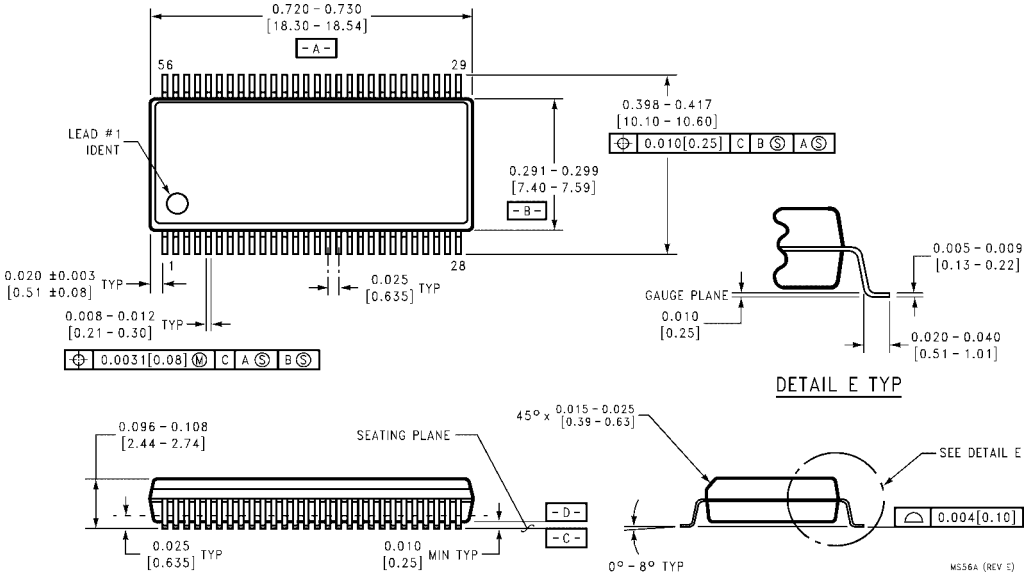


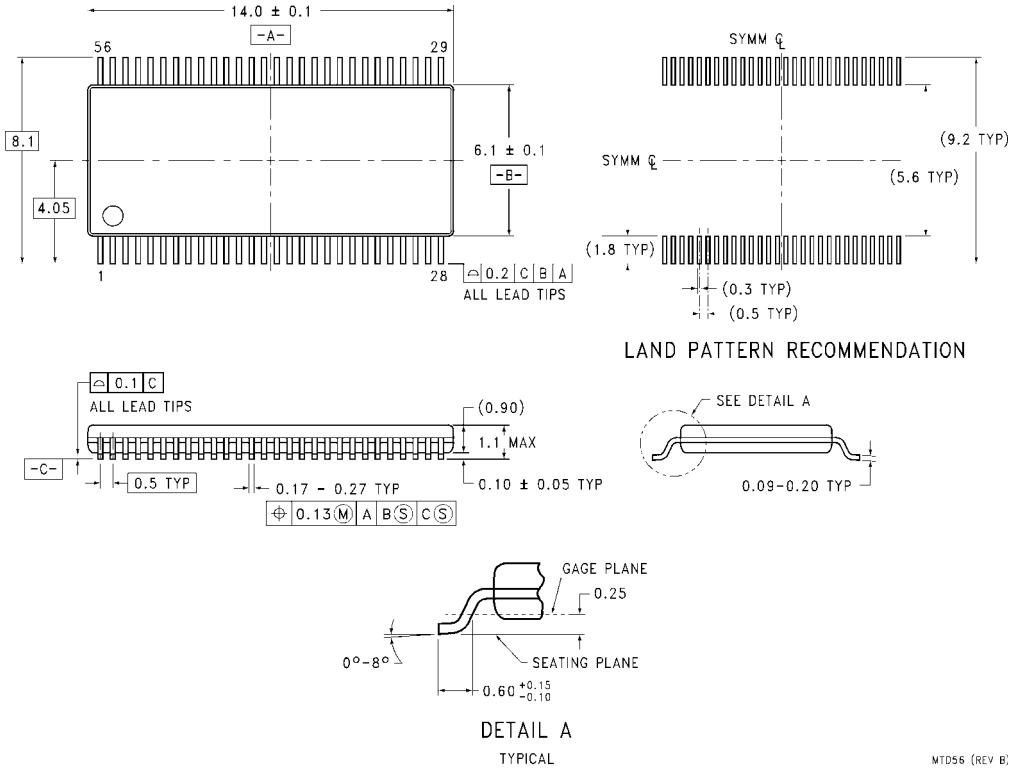
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

September 1991
Revised January 2000

74ACTQ18825
18-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACTQ18825 contains eighteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 18-bit operation.

The ACTQ18825 utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector for superior performance.

Features

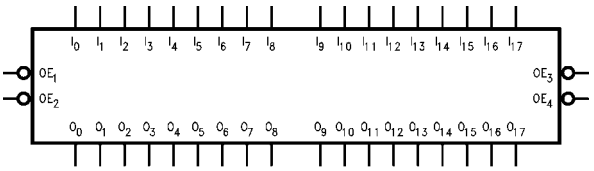
- Utilizes Fairchild FACT Quiet Series technology
- Broadside pinout allows for easy board layout
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Separate control logic for each byte
- Extra data width for wider address/data paths or buses carrying parity
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loading specs for both 50 pF and 250 pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ18825SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ18825MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

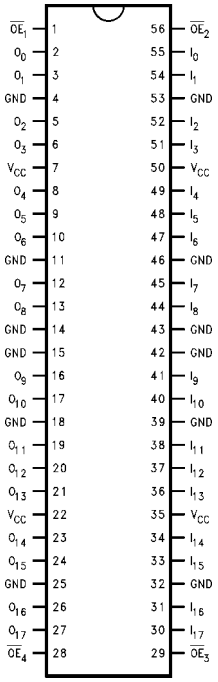


Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{17}	Inputs
O_0–O_{17}	Outputs

FACT™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Connection Diagram



Functional Description

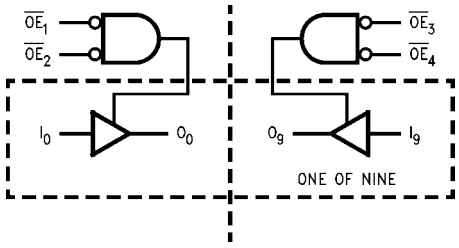
The ACTQ18825 contains eighteen non-inverting buffers with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independently of the other. The control pins may be shorted together to obtain full 18-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each byte. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Truth Table

Inputs						Outputs	
Byte 1 (0:8)		Byte 2 (8:17)		I_0–I_8	I_9–I_{17}	O_0–O_8	O_9–O_{17}
$\overline{OE}_1$	$\overline{OE}_2$	$\overline{OE}_3$	$\overline{OE}_4$				
L	L	L	L	H	H	H	H
H	X	L	L	X	L	Z	L
X	H	L	L	X	H	Z	H
L	L	H	X	L	X	L	Z
L	L	X	H	H	X	H	Z
H	H	H	H	X	X	Z	Z
L	L	L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} +0.5V	+20 mA
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
Per Output Pin	±50 mA
Storage Temperature	−65°C to +150°C
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} −0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} −2.1V
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 2)				−75	mA	V_{OHD} = 3.85V Min
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−0.8		V	Figure 1, Figure 2 (Note 5)(Note 6)
V_{OHP}	Maximum Overshoot	5.0	V_{OH} + 1.0	V_{OH} + 1.5		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{OHV}	Minimum V_{CC} V_{CC} Droop	5.0	V_{OH} − 1.0	V_{OH} − 1.8		V	Figure 1, Figure 2 (Note 4)(Note 6)
V_{IHD}	Minimum HIGH Dynamic Input Voltage Level	5.0	1.7	2.0		V	(Note 4)(Note 7)
V_{ILD}	Maximum LOW Dynamic Input Voltage Level	5.0	1.2	0.8		V	(Note 4)(Note 7)

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Worst case package.

Note 5: Maximum number of outputs that can switch simultaneously is n. (n-1) outputs are switched LOW and one output held LOW.

Note 6: Maximum number of outputs that can switch simultaneously is n. (n-1) outputs are switched HIGH and one output held HIGH.

Note 7: Maximum number of data inputs (n) switching (n-1) input switching 0V to 3V. Input under test switching 3V to threshold (VILD).

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	5.0	2.0	5.3	8.4	2.0	9.0	ns
t_{PLH}	Data to Output		2.0	5.6	8.7	2.0	9.2	
t_{PZL}	Output Enable	5.0	2.0	6.3	9.6	2.0	10.3	ns
t_{PZH}	Time		2.0	6.5	9.7	2.0	10.4	
t_{PLZ}	Output Disable	5.0	1.5	4.5	7.3	1.5	7.6	ns
t_{PHZ}	Time		1.5	5.1	8.5	1.5	8.8	

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, V_{CC} = Com, $C_L = 50$ pF, 16 Outputs Switching (Note 9)			$T_A = -40°C$ to $+85°C$, V_{CC} = Com, $C_L = 250$ pF (Note 10)		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	6.5	8.0	9.8			ns
t_{PHL}	Data to Output	5.5	6.5	8.9			
t_{PZH}	Output Enable Time	6.1	7.6	9.2	(Note 11)		ns
t_{PZL}		6.5	7.8	9.4			
t_{PHZ}	Output Disable Time	3.1	5.0	6.1	(Note 12)		ns
t_{PLZ}		3.5	5.2	6.5			
t_{OSHL} (Note 13)	Pin to Pin Skew HL Data to Output			1.5			ns
t_{OSLH} (Note 13)	Pin to Pin Skew LH Data to Output			2.0			ns
t_{OST} (Note 13)	Pin to Pin Skew LH/HL Data to Output			2.0			ns

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 12: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 13: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t_{OST}).

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Pin Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	95	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

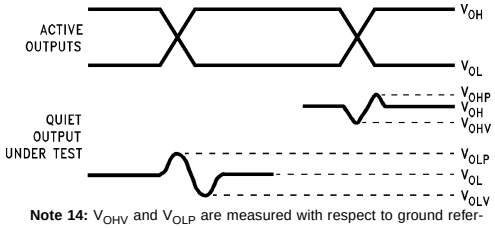
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



Note 14: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 15: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

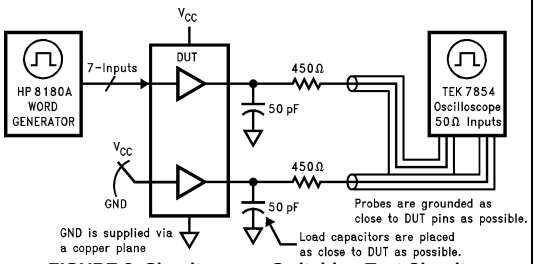
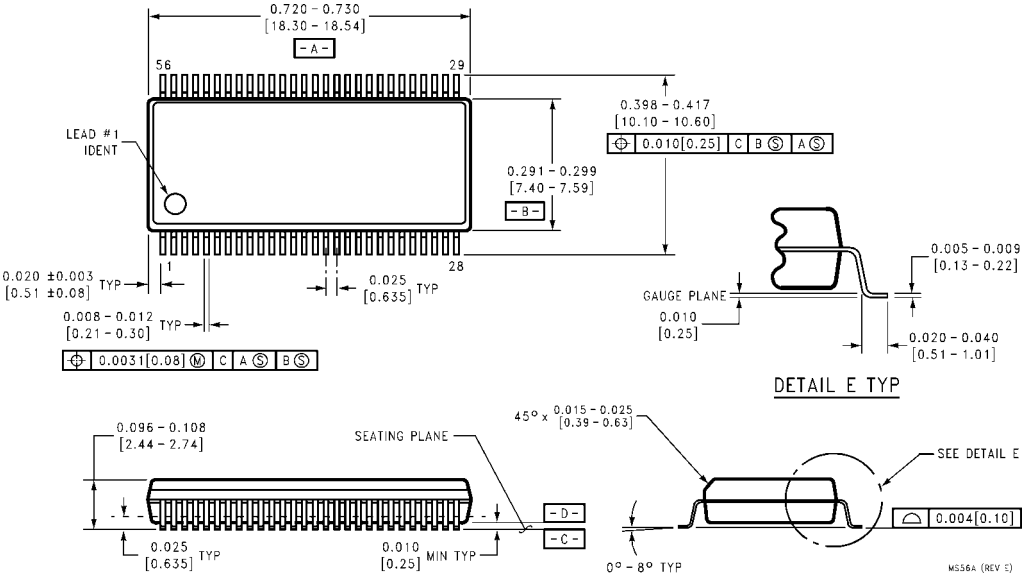


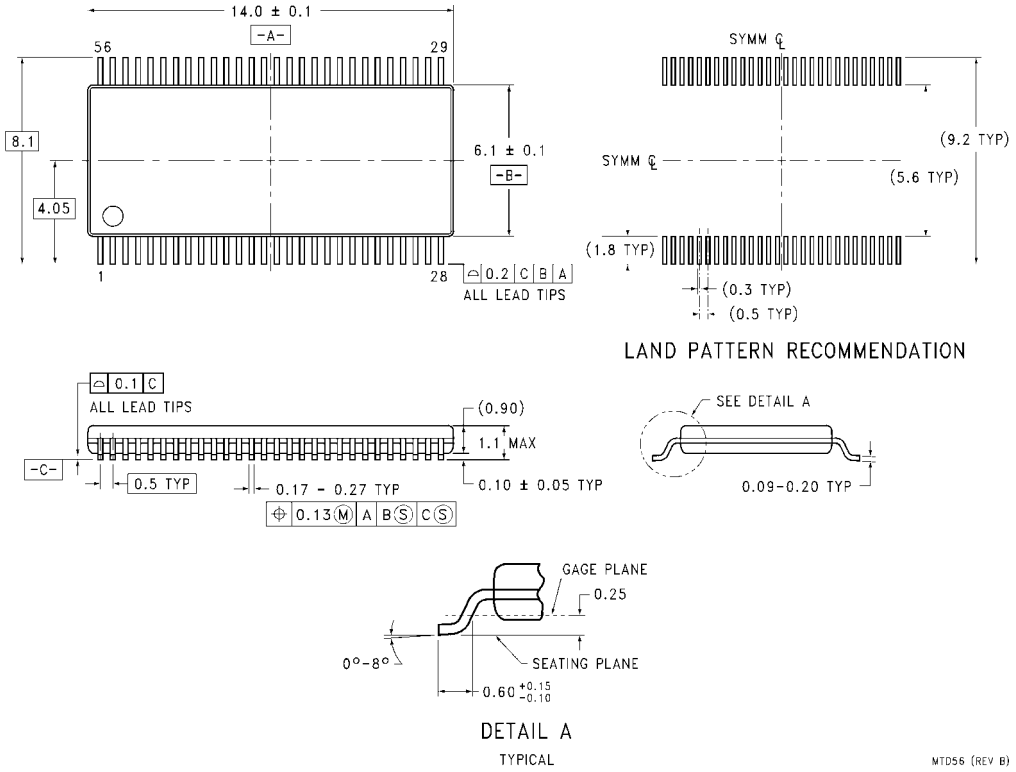
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1989
Revised November 1999

74ACTQ273
Quiet Series Octal D-Type Flip-Flop

General Description

The ACTQ273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) input load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D-type input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

The ACTQ utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

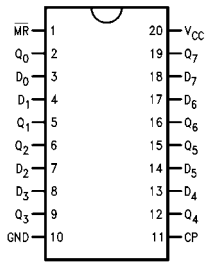
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- Buffered common clock and asynchronous master reset
- Outputs source/sink 24 mA
- 4 kV minimum ESD immunity

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ273SC	M20B	20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300" Wide Body
74ACTQ273SJ	M20D	20-Lead Small Outline Package, EIAJ TYPE II, 5.3mm Wide
74ACTQ273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACTQ273PC	N20A	20-Lead Plastic Dual-In-Line Package, JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

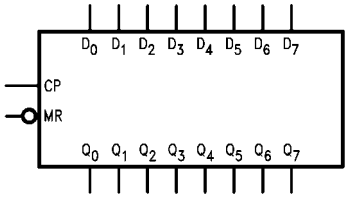


Pin Descriptions

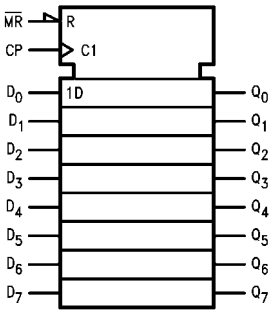
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

FACT™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Logic Symbols



IEEE/IEC

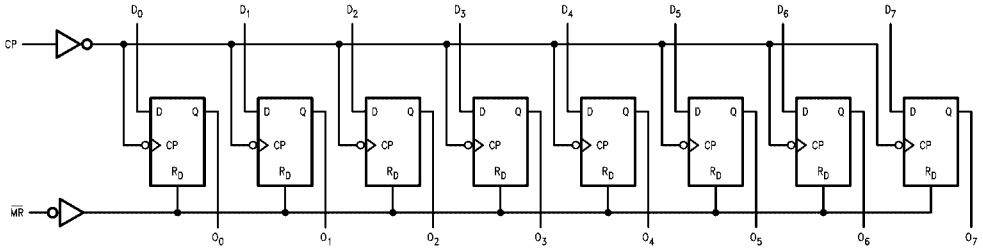


Mode Select-Function Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load “1”	H	⌐	H	H
Load “0”	H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1Figure 2 (Note 4)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1Figure 2 (Note 4)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 5)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 5)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Max number of outputs defined as (n). n − 1 Data inputs are driven 0V to 3V; one output @ GND.

Note 5: Max number of Data Inputs (n) switching. (n − 1) Inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}) f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	125	189		110		MHz
t_{PLH} t_{PHL}	Propagation Delay CP to Q_n	5.0	1.5	6.5	8.5	1.5	9.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	1.5	7.0	9.0	1.5	9.5	ns
t_{OSHL}, t_{OSLH}	Output to Output Skew (Note 7)	5.0		0.5	1.0		1.0	ns

Note 6: Voltage Range 5.0 is 5.0V ± 0.5V

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum	
t_S	Setup Time, HIGH or LOW D_n to CP	5.0	1.0	3.5	3.5	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	−0.5	1.5	1.5	ns
t_W	Clock Pulse Width HIGH or LOW	5.0	2.0	4.0	4.0	ns
t_W	$\overline{MR}$ Pulse Width HIGH or LOW	5.0	1.5	4.0	4.0	ns
t_W	Recovery Time $\overline{MR}$ to CP	5.0	0.5	3.0	3.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

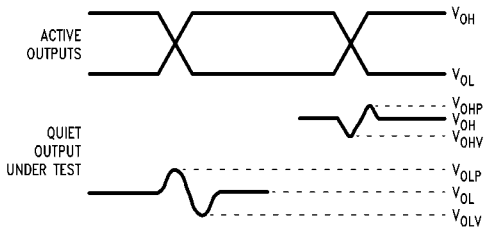


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 9: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 10: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

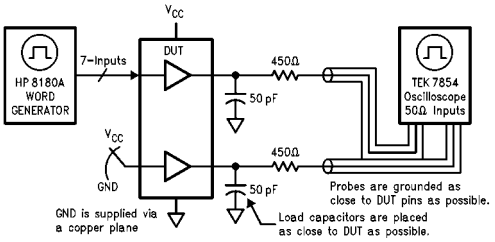
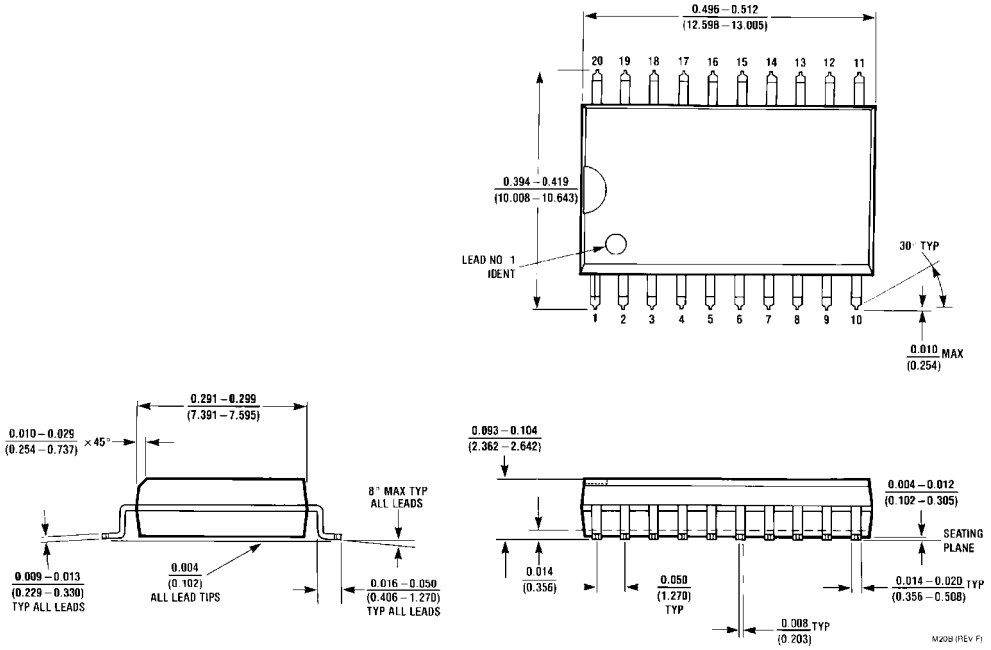


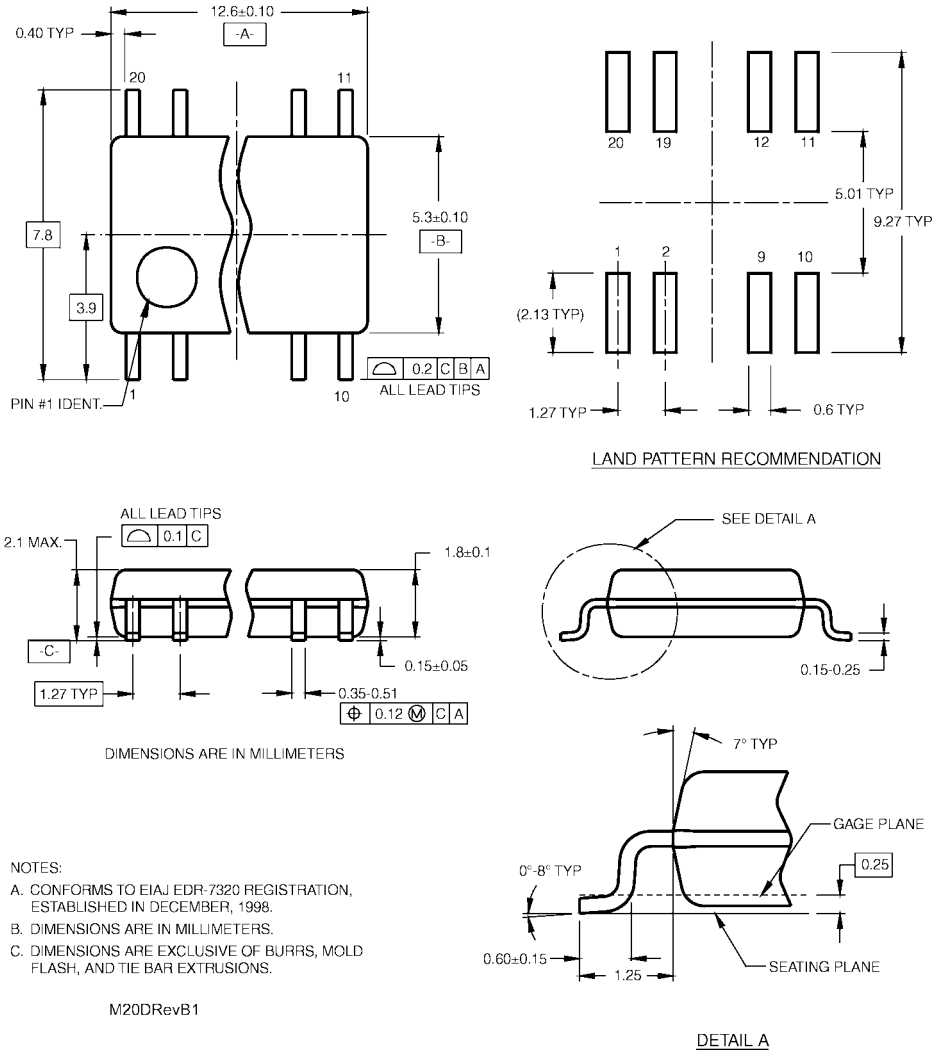
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300” Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

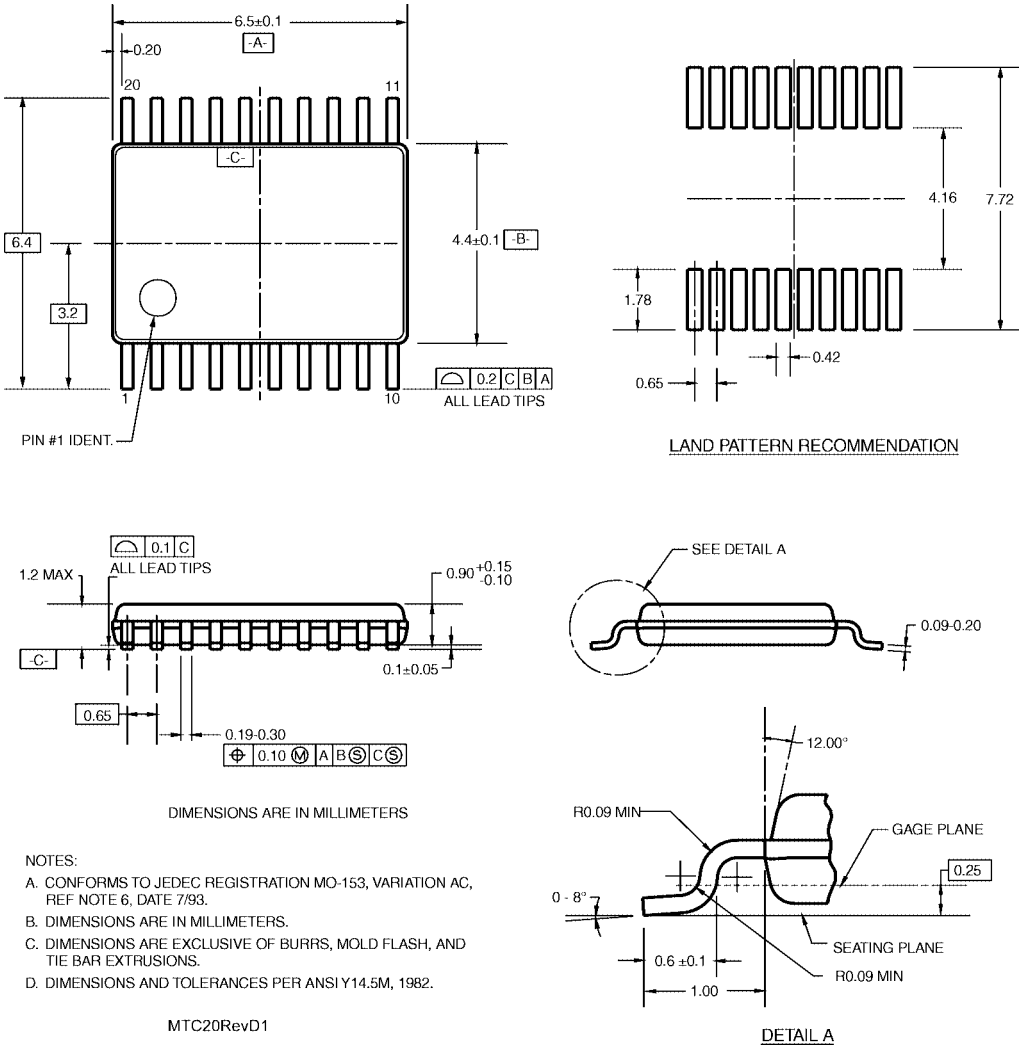
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

20-Lead Small Outline Package, EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

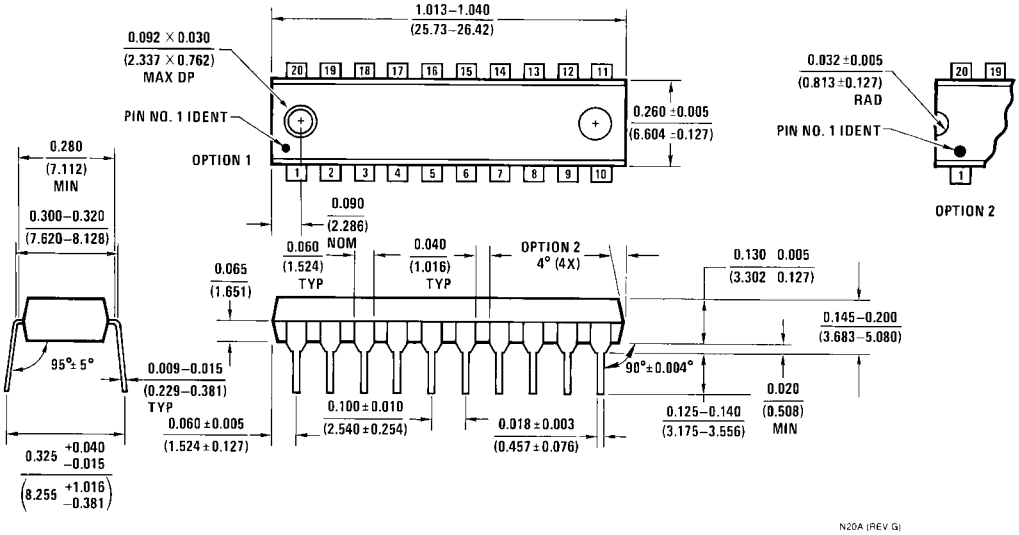
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package, JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1993
Revised June 1999

74ACTQ32
Quiet Series Quad 2-Input OR Gate

General Description

The ACTQ320 contains four, 2-input OR gates and utilizes Fairchild Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

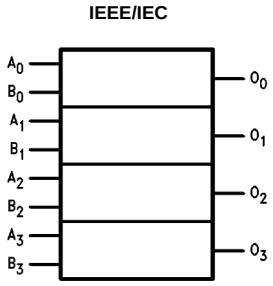
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Minimum 4 kV ESD protection
- TTL-compatible inputs
- Outputs source/sink 24 mA

Ordering Code:

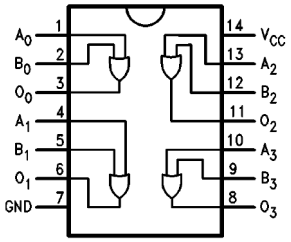
Order Number	Package Number	Package Description
74ACT10SC	M14A	14-Lead (0.150' Wide) Molded Small Outline Package, JEDEC, SOIC
74ACT10PC	N14A	14-Lead (0.300' Wide) Molded Dual-in-Line Package, PDIP

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Descriptions
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

FACT™, FACT Quiet Series™, and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J) PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside of databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −55°C to +125°C Guaranteed Limits		T_A = −40°C to +85°C Guaranteed Limits	Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4	5.4		
							V	V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.70	3.76		I_{OH} = − 24 mA
		5.5		4.86	4.70	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1	0.1		
							V	V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.50	0.44		I_{OL} = 24 mA
		5.5		0.36	0.50	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	±1.0	± 1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.6	1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			50	75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−50	−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	40.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5			V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2			V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2			V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8			V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP Package.

Note 5: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n-1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHZ.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	5.0	2.5	6.0	6.5	2.5	7.0	ns
t_{PHL}	Propagation Delay Data to Output	5.0	2.0	6.0	6.5	2.5	7.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	68	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment

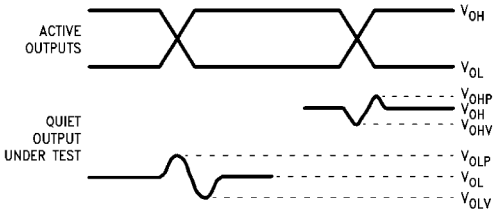
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACTQ devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

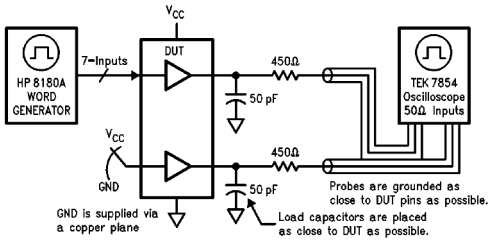
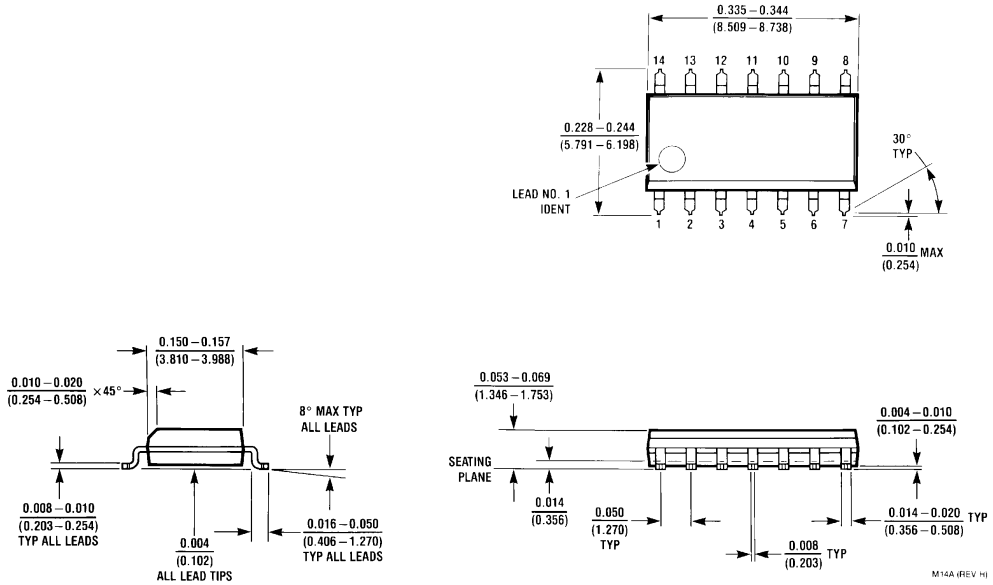


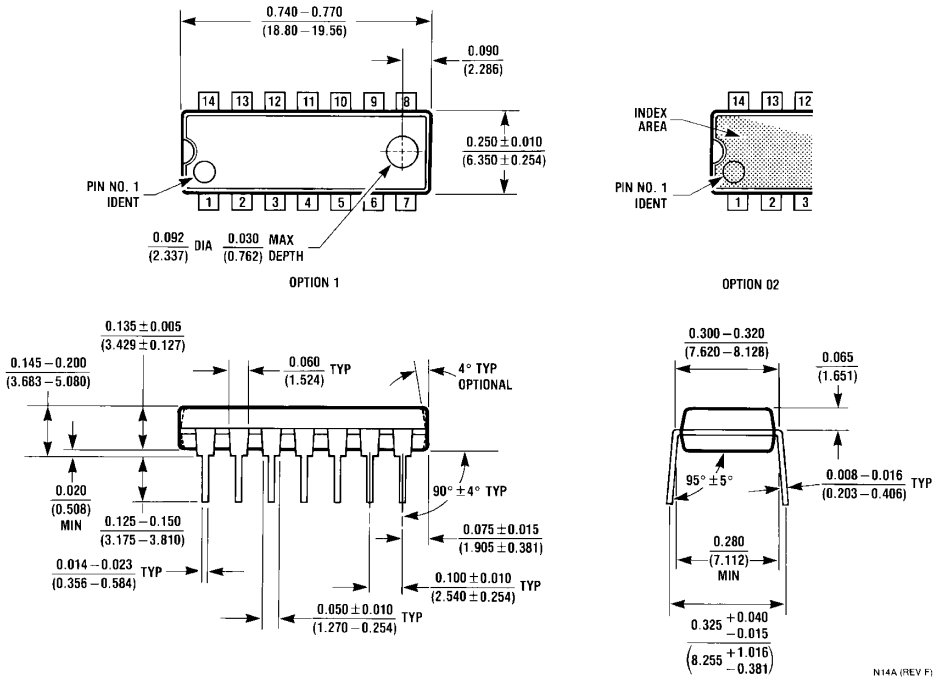
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD
SEMICONDUCTOR™

March 1999
Revised March 1999

Document Update In Progress

This document is currently in the process of being updated.

A new document will be posted to the web site when it is completed.

Please contact the Fairchild Customer Support Center or your local Fairchild Representative if your need for this information is urgent.

We apologize for the inconvenience.

Document Update In Progress

FAIRCHILD SEMICONDUCTOR™

January 1990
Revised November 1999

74ACTQ533
Quiet Series Octal Transparent Latch with 3-STATE Outputs

General Description

The ACTQ533 consists of eight latches with 3-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the bus output is in the high impedance state.

The ACTQ533 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

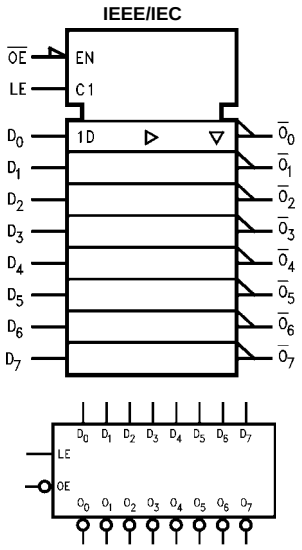
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch up immunity
- Eight latches in a single package
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Inverted version of the ACTQ373
- 4 kV minimum ESD immunity

Ordering Code:

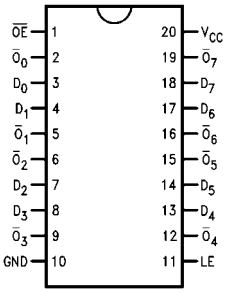
Order Number	Package Number	Package Description
74ACTQ533SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ533MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACTQ533PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
$\overline{O}_0$–$\overline{O}_7$	3-STATE Latch Outputs

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Truth Table

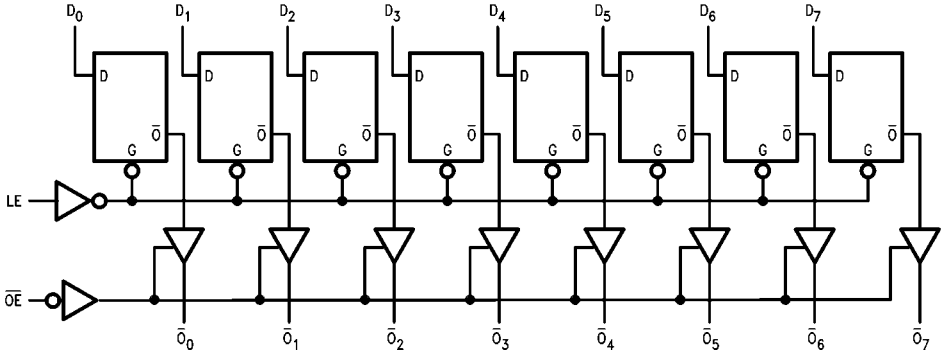
Inputs			Outputs
LE	$\overline{OE}$	D_n	$\overline{O}_n$
X	H	X	Z
H	L	L	H
H	L	H	L
L	L	X	$\overline{O}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
$\overline{O}_0$ = Previous $\overline{O}_0$ before HIGH-to-LOW transition of Latch Enable

Functional Description

The ACTQ533 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	− 0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	− 20 mA
V_I = V_{CC} + 0.5V	+ 20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = − 0.5V	− 20 mA
V_O = V_{CC} + 0.5V	+ 20 mA
DC Output Voltage (V_O)	− 0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	− 65°C to + 150°C
DC Latchup Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figures 1, 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figures 1, 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Typ	Guaranteed Limits			
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n–1) inputs switching 0V to 3V Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay D_n to O_n	5.0	2.0	6.0	8.0	2.0	8.5	ns
t_{PHL} t_{PLH}	Propagation Delay LE to O_n	5.0	2.5	7.0	9.0	2.5	9.5	ns
t_{PZL}, t_{PZH}	Output Enable Time	5.0	2.0	7.0	9.0	2.0	9.5	ns
t_{PHZ}, t_{PLZ}	Output Disable Time	5.0	1.0	8.0	10.0	1.0	10.5	ns
t_{OSHL} t_{OSLH}	Output to Output Skew D_n to O_n(Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0	0	1.5	1.5	ns
t_W	LE Pulse Width, HIGH	5.0	2.0	4.0	4.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	40	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with a digital volt meter.

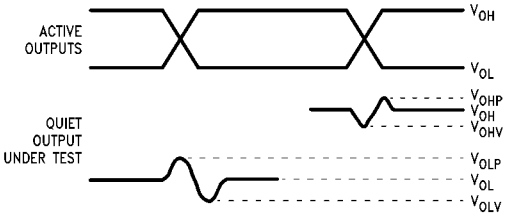


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 10: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 11: Input pulses have the following characteristics:

f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level on the V_{IH} until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

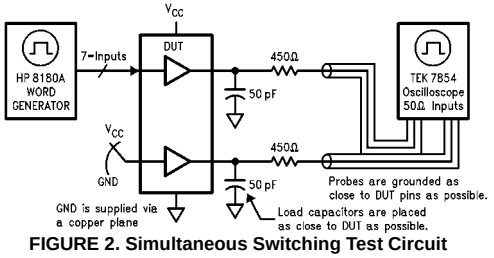
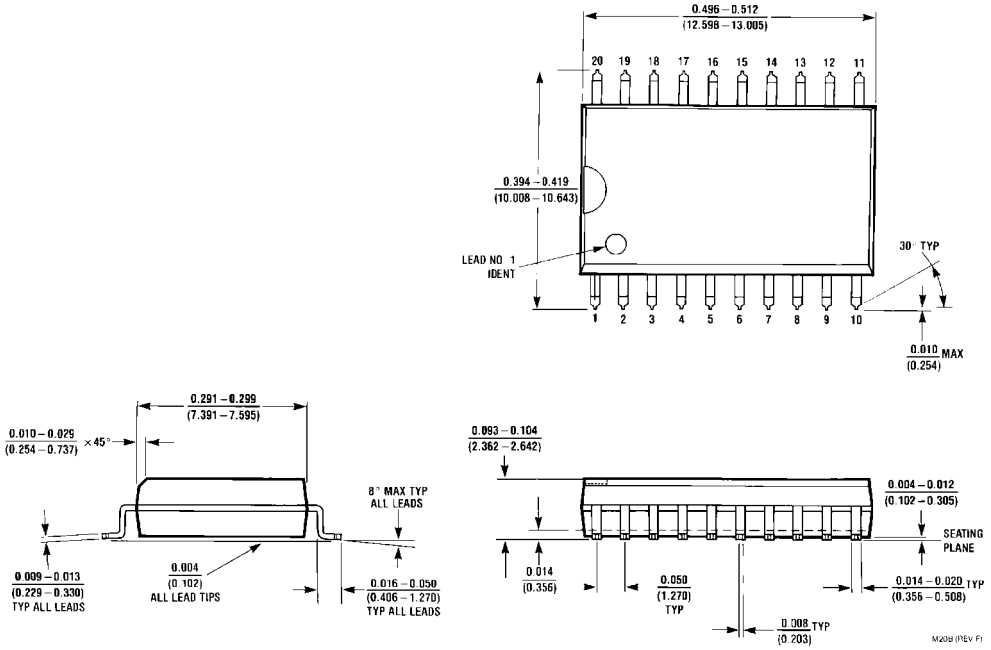


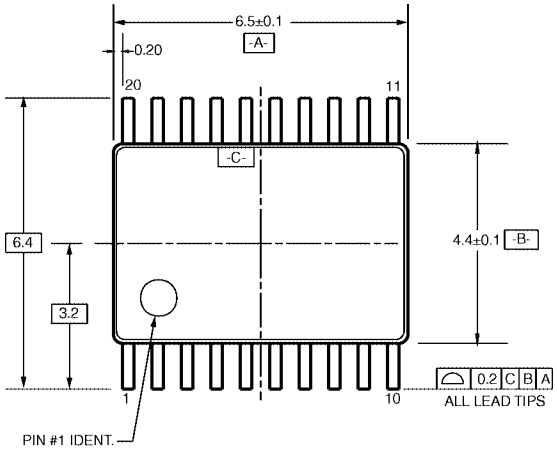
FIGURE 2. Simultaneous Switching Test Circuit

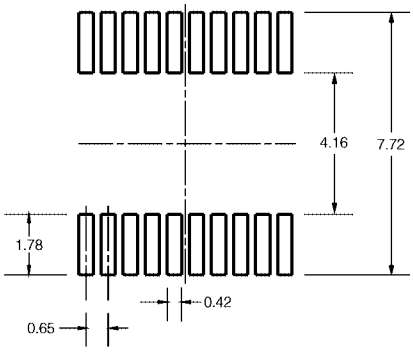
Physical Dimensions inches (millimeters) unless otherwise noted



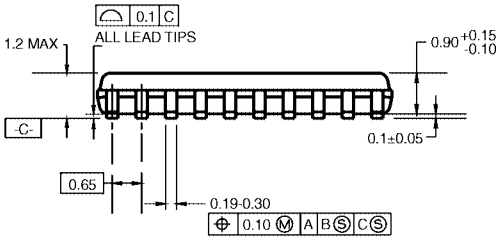
20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M20B

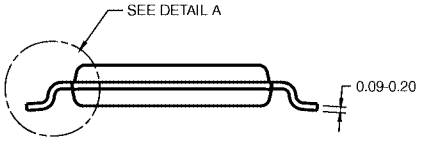
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS

NOTES:

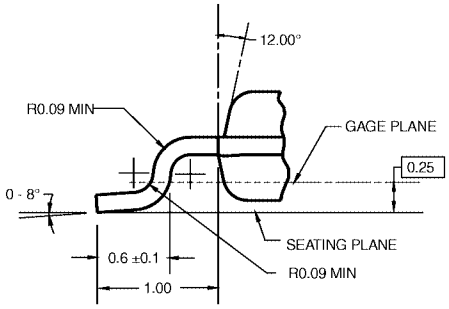
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

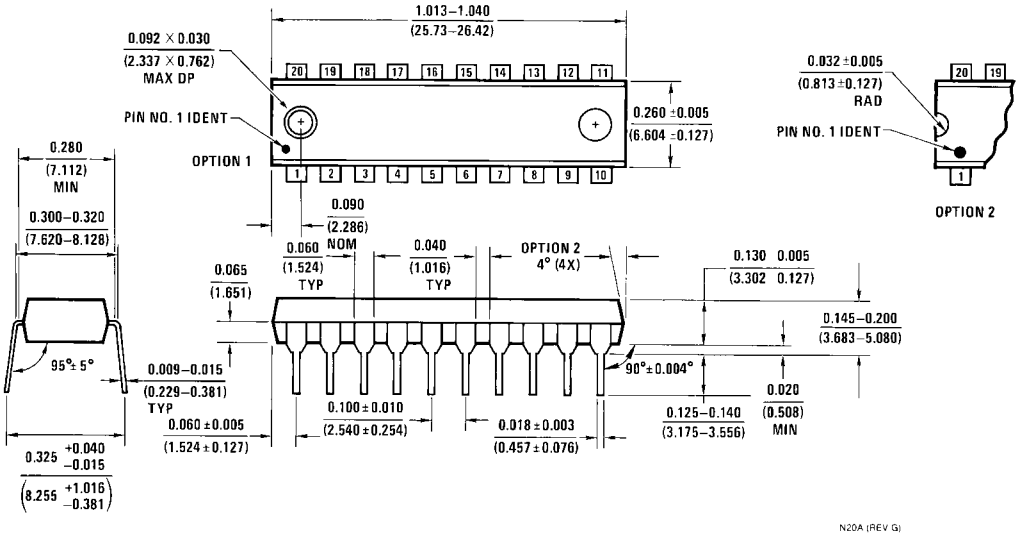
MTC20RevD1



DETAIL A

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1993
Revised November 1999

74ACTQ541
Quiet Series Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The 74ACTQ541 is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

This device is similar in function to the 74ACTQ244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

The 74ACTQ541 utilizes FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to split ground bus for superior performance.

Features

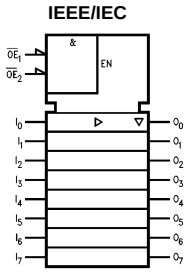
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of package for easy board layout
- Non-inverting 3-STATE outputs
- Guaranteed 4 kV minimum ESD immunity
- TTL compatible inputs
- Outputs source/sink 24 mA

Ordering Code:

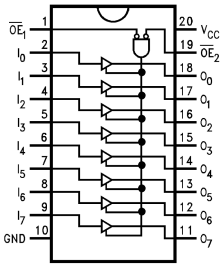
Order Number	Package Number	Package Description
74ACTQ541SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74ACTQ541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACTQ541PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the order code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Name	Pin Description
$\overline{OE}_1 - \overline{OE}_2$	3-STATE Output Enable (Active-LOW)
$I_0 - I_7$	Inputs
$O_1 - O_7$	Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	140°C

Recommended Operating Conditions

Supply Voltage V_{CC}	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4		
		4.5		3.86	3.76	V	V_{IN} = V_{IL} or V_{IH} (Note 2) I_{OH} = −24 mA
		5.5		4.86	4.76		−24 mA
V_{OL}	Maximum LOW Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 2) I_{OH} = 24 mA
		5.5		0.36	0.44		24 mA
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 3)	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Plastic DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of Data Inputs (n) switching. (n−1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	5.0	2.0	4.5	7.0	2.0	7.5	ns
t_{PHL}	Data to Output		2.0	5.5	7.0	2.0	7.5	
t_{PZH}	Output Enable Time	5.0	2.0	5.0	9.0	2.0	9.5	ns
t_{PZL}			2.0	6.5	9.0	2.0	9.5	
t_{PHZ}	Output Disable Time	5.0	1.5	5.5	7.5	1.5	8.0	ns
t_{PLZ}			1.5	5.5	7.5	1.5	8.0	
t_{OSHL}	Output to Output			0.5	1.0		1.0	ns
t_{OSLH}	Skew Data to Output (Note 8)			0.5	1.0		1.0	

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	70	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

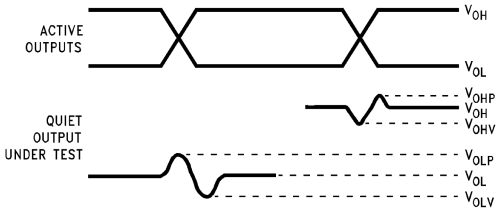
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



$V_{OHV}$and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability on the measurements.

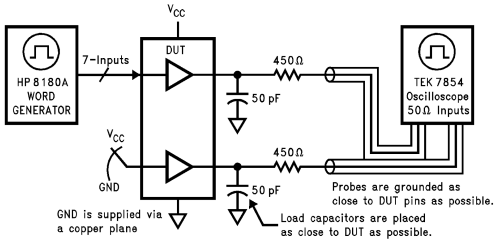
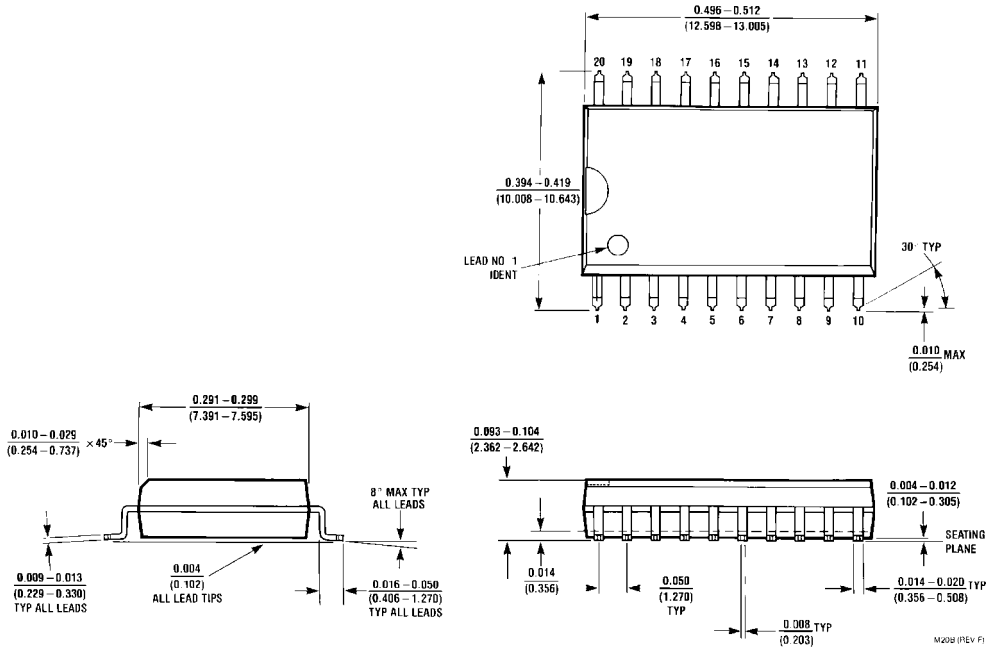


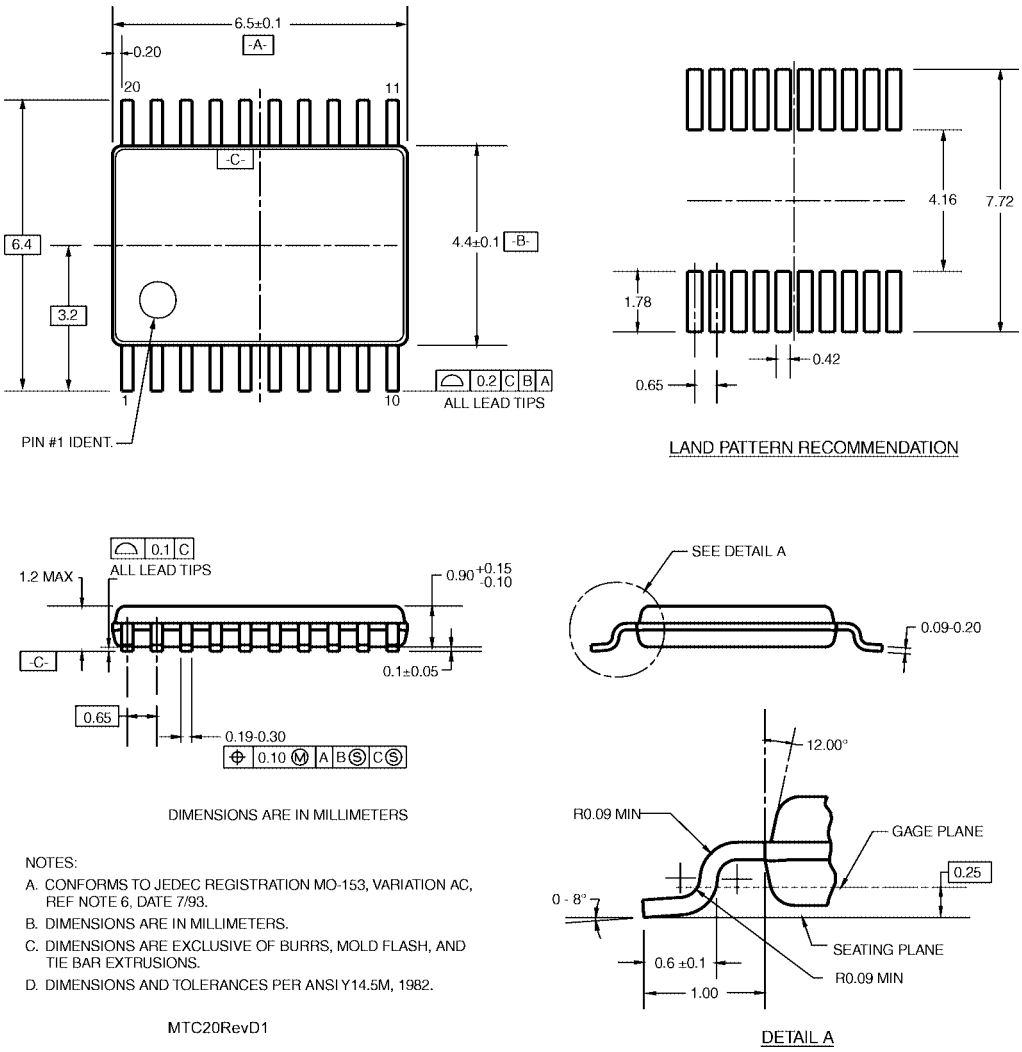
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

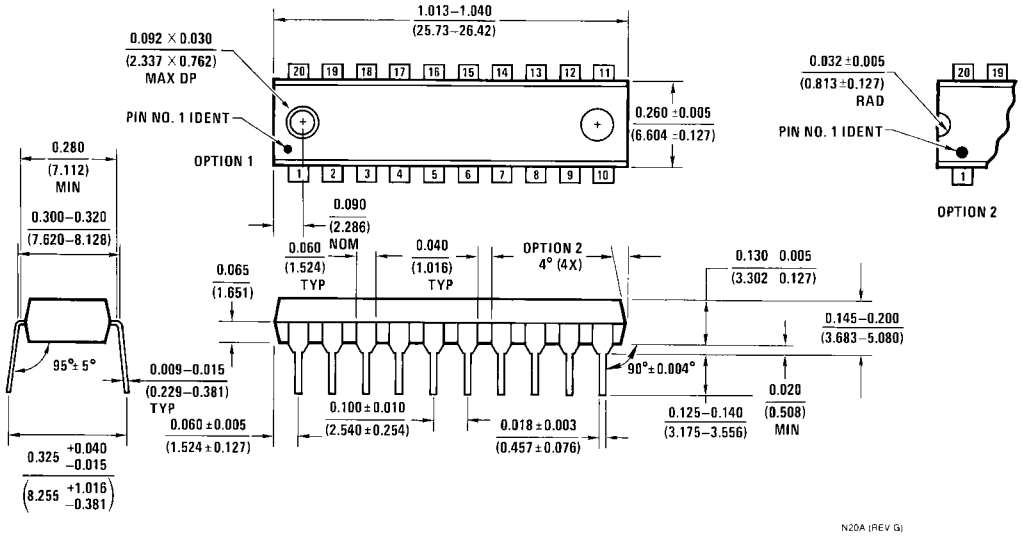
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1990
Revised December 1998

74ACTQ563
Quiet Series™ Octal Latch with 3-STATE Outputs

General Description

The ACTQ563 is a high speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs. The ACTQ563 is functionally identical to the ACTQ573, but with inverted outputs. The ACTQ563 utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

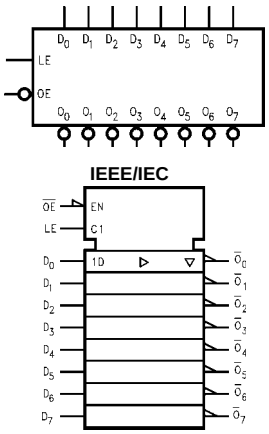
- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Outputs source/sink 24 mA
- Faster prop delays than standard ACT563
- Functionally identical to the ACTQ573 but with inverted outputs

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ563PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

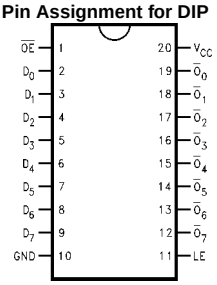
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram

Pin Assignment for DIP



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
$\overline{O}_0$–$\overline{O}_7$	3-STATE Latch Outputs

Functional Description

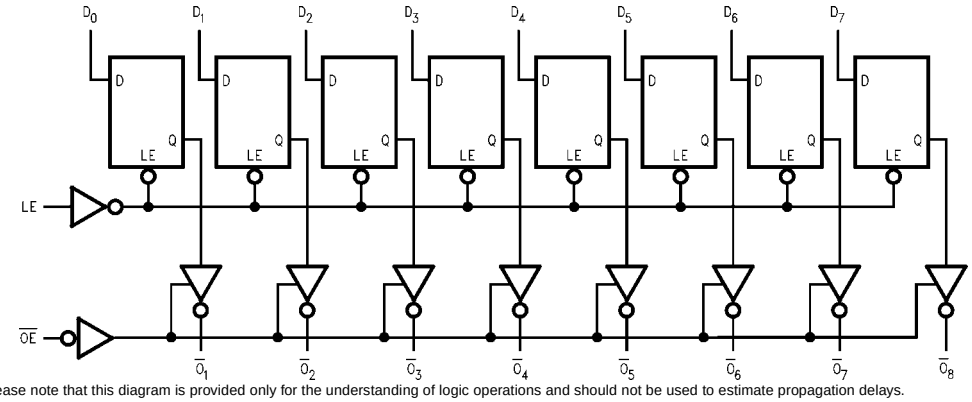
The ACTQ563 contains eight D-type latches with 3-STATE complementary outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but that does not interfere with entering new data into the latches.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	LE	D	Q	$\overline{O}$	
H	X	X	X	Z	High-Z
H	H	L	H	Z	High-Z
H	H	H	L	Z	High-Z
H	L	X	NC	Z	Latched
L	H	L	H	H	Transparent
L	H	H	L	L	Transparent
L	L	X	NC	NC	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latchup Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I_{OUT} = − 50 µA
	Output Voltage	5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1		I_{OUT} = 50 µA
	Output Voltage	5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE	5.5		± 0.25	± 2.5	µA	$V_I = V_{IL}$, V_{IH}
	Leakage Current						$V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output	5.0	1.1	1.5		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 4)(Note 5)
V_{OLV}	Quiet Output	5.0	−0.6	−1.2		V	Figure 1, Figure 2
	Minimum Dynamic V_{OL}						(Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

DC Electrical Characteristics (Continued)

Note 6: Max number of data inputs (n) switching. (n–1) inputs switching 0V to 3V. Input-under-test switching; 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	3.3	2.5	8.5	11.5	2.5	12.0	ns
t_{PLH}	D_n to O_n	5.0	1.5	5.5	7.5	1.5	8.0	
t_{PLH}	Propagation Delay	3.3	2.5	8.5	13.0	2.5	13.5	ns
t_{PHL}	LE to O_n	5.0	2.0	6.0	8.5	2.0	9.0	
t_{PZL}	Output Enable Time	3.3	2.5	8.5	13.0	2.5	13.5	ns
t_{PZH}		5.0	1.5	6.0	8.5	1.5	9.0	
t_{PHZ}	Output Disable Time	3.3	1.0	9.0	14.5	1.0	15.0	ns
t_{PLZ}		5.0	1.0	6.5	9.5	1.0	10.0	
t_{OSHL}	Output to Output Skew (Note 8)	3.3		1.0	1.5		1.5	ns
t_{OSLH}	D_n to O_n	5.0		0.5	1.0		1.0	

Note 7: Voltage Range 5.0 is 5.0V ±0.5V and 3.3 is 3.3V ± 0.3V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	3.3	0	3.0	3.0	ns
	D_n to LE	5.0	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	3.3	0	1.5	1.5	ns
	D_n to LE	5.0	0	1.5	1.5	
t_W	LE Pulse Width, HIGH	3.3	2.0	4.0	4.0	ns
		5.0	2.0	4.0	4.0	

Note 9: Voltage Range 5.0 is 5.0V ±0.5V and 3.3V is 3.3 ± 0.3V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	42	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

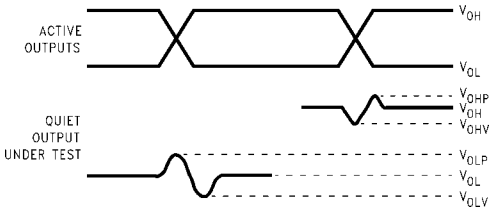
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics:

f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with a n oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

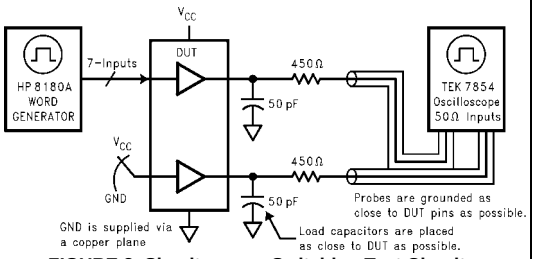
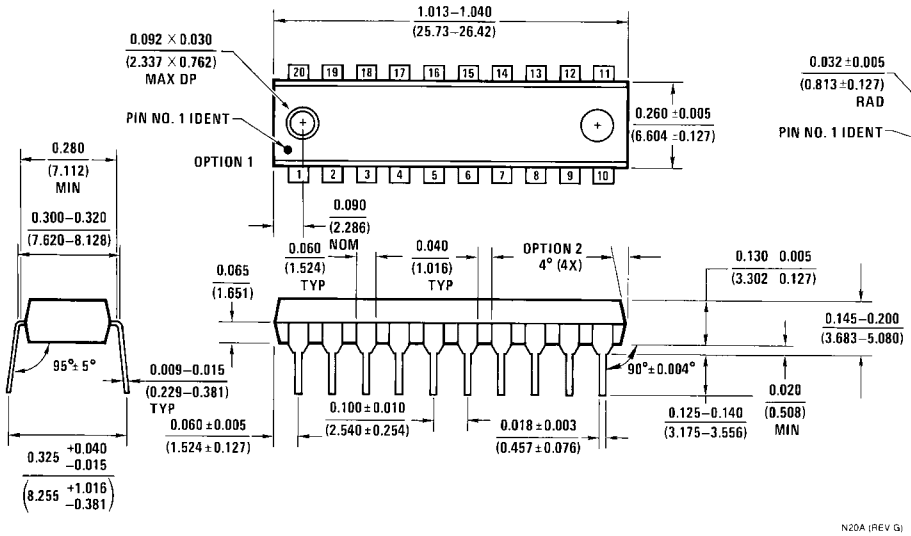


FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

June 1991
Revised November 1999

74ACTQ652
Quiet Series™ Transceiver/Register

General Description

The ACTQ652 consists of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to the HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function.

The ACTQ652 utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to split ground bus for superior performance.

Features

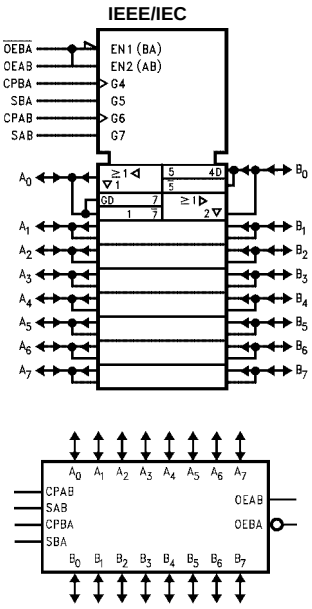
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- Outputs source/sink 24 mA
- TTL-compatible inputs

Ordering Code:

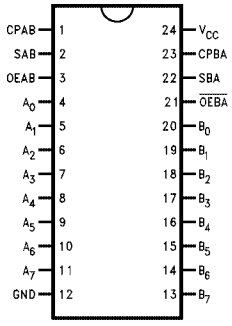
Order Number	Package Number	Package Description
74ACTQ652SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ652MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74ACTQ652SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7, B_0–B_7	A and B Inputs/3-STATE Outputs
CPAB, CPBA	Clock Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{OEBA}$	Output Enable Inputs

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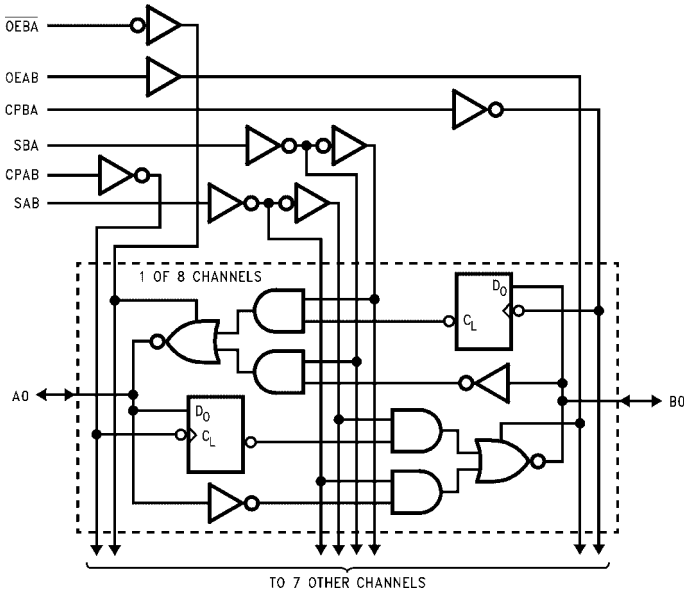
Function Table

Inputs						Inputs/Outputs (Note 1)		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

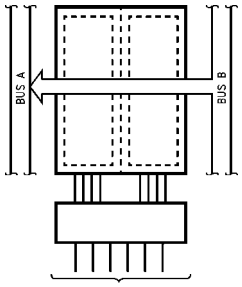
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in Figure 1 demonstrate the four fundamental bus-management functions that can be performed with the Octal bus transceivers and receivers.

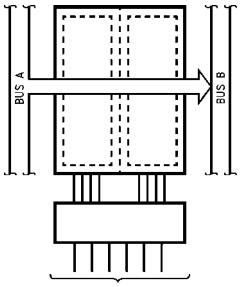
Data on the A or B data bus, or both can be stored in the internal D-type flip-flop by LOW-to-HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and $\overline{\text{OEBA}}$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Note A: Real-Time Transfer Bus B to Bus A



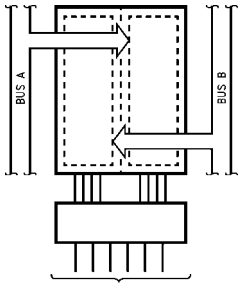
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Note B: Real-Time Transfer Bus A to Bus B



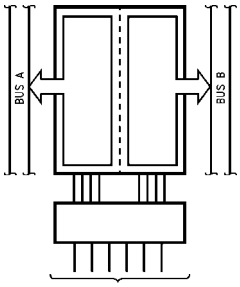
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

Note C: Storage



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
X	H	⌐	X	X	X
L	X	X	⌐	X	X
L	H	⌐	⌐	X	X

Note D: Transfer Storage Data to A or B



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

FIGURE 1.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 3)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 3)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZT}	Maximum I/O Leakage Current	5.5		± 0.6	± 6.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 4)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Maximum HIGH Level Output Noise	5.0	1.1	1.5		V	Figure 2Figure 3 (Note 5)(Note 6)
V_{OLV}	Maximum LOW Level Output Noise	5.0	−0.6	−1.2		V	Figure 2Figure 3 (Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 5)(Note 7)

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 5)(Note 7)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: PDIP package.

Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 7: Max number of data inputs (n) switching. (n – 1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF Min	Typ	Max	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF Min	Max	Units
f_{MAX}	Maximum Clock Frequency	5.0						MHz
t_{PLH} t_{PHL}	Propagation Delay Clock to Bus	5.0	2.0	7.0	9.5	2.0	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay Bus to Bus	5.0	2.0	6.5	9.0	2.0	9.5	ns
t_{PLH} t_{PHL}	Propagation Delay SBA or SAB to A or B	5.0	2.5	6.5	10.0	2.5	10.5	ns
t_{PZH} t_{PZL}	Enable Time OEBA to A (Note 8)	5.0	2.0	7.0	10.5	2.0	11.0	ns
t_{PHZ} t_{PLZ}	Disable Time OEBA to A (Note 8)	5.0	1.0	5.0	8.0	1.0	8.5	
t_{PZH} t_{PZL}	Enable Time OEAB to B	5.0	2.0	7.0	10.5	2.0	11.0	
t_{PHZ} t_{PLZ}	Disable Time OEAB to B	5.0	1.0	5.0	8.0	1.0	8.5	ns
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW, Bus to Clock	5.0	3.0			3.0		ns
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW, Bus to Clock	5.0	1.5			1.5		ns
$t_w(H)$ $t_w(L)$	Clock Pulse Width HIGH or LOW	5.0	4.0			4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9) A to B, B to A or Clock to Output	5.0		0.5	1.0		1.0	ns

Note 8: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any separate outputs of the same device. The specification applies to any output switching in the same direction, either HIGH-to-LOW (T_{OSHL}) or LOW-to-HIGH (T_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C_{PD}	Power Dissipation Capacitance	54	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

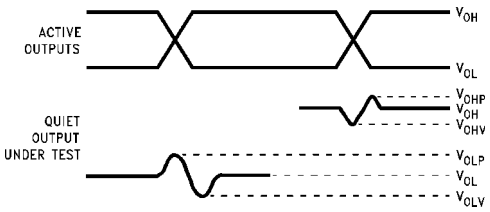
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note A: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note B: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 2. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV}on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH} until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

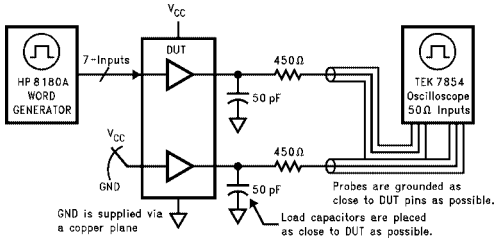
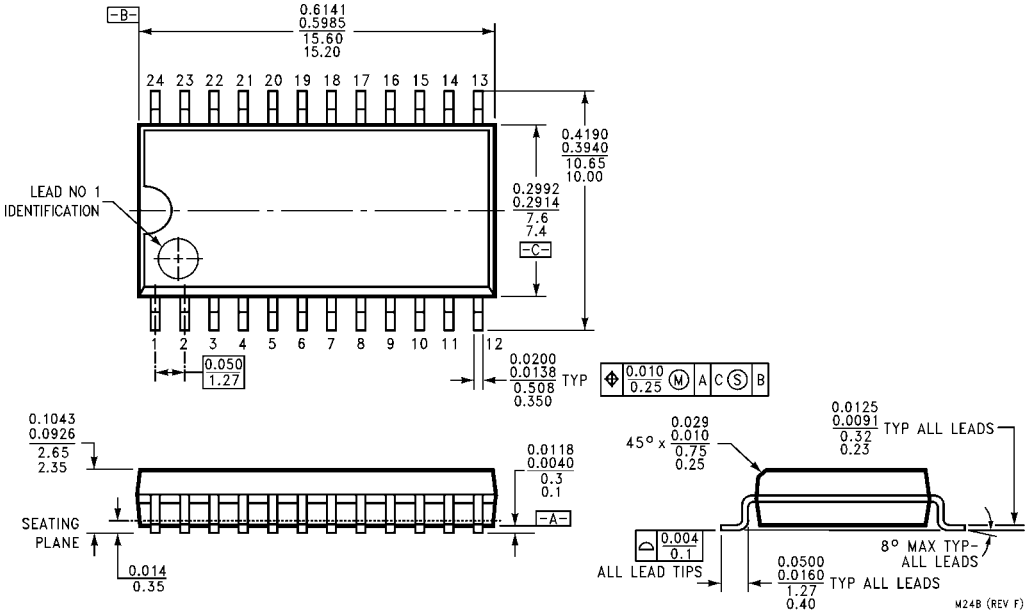


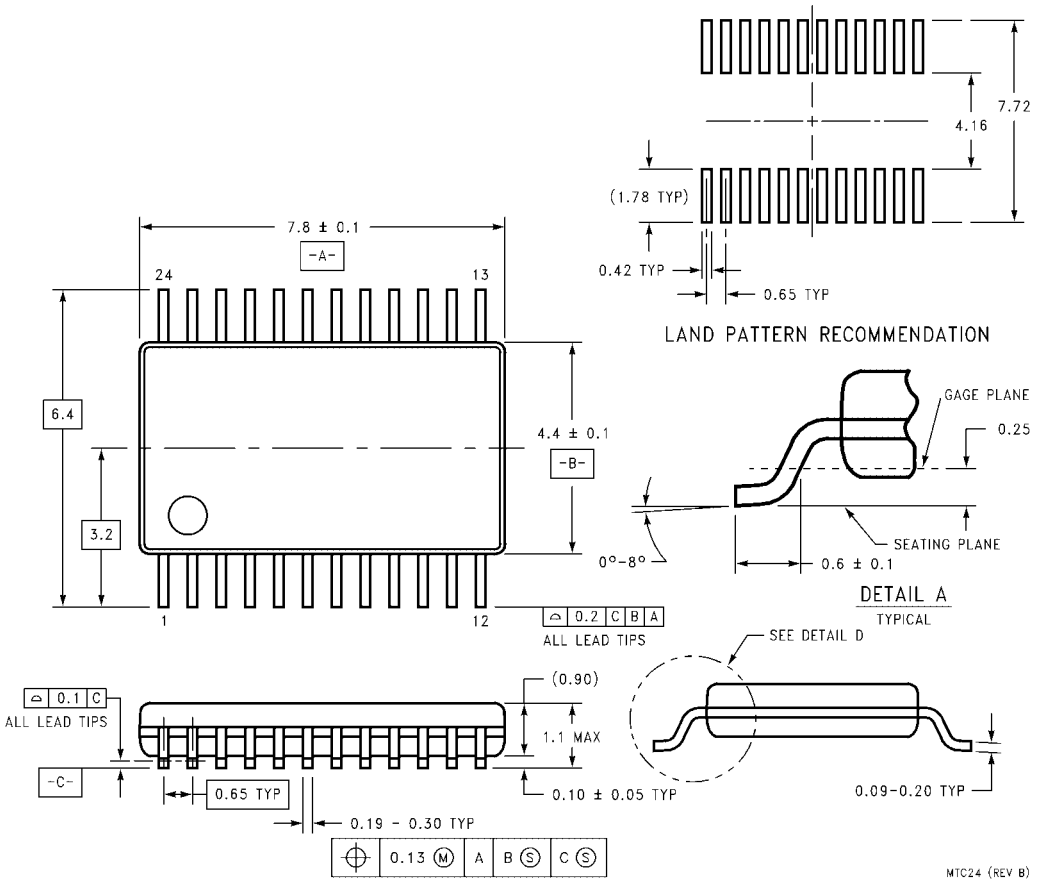
FIGURE 3. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



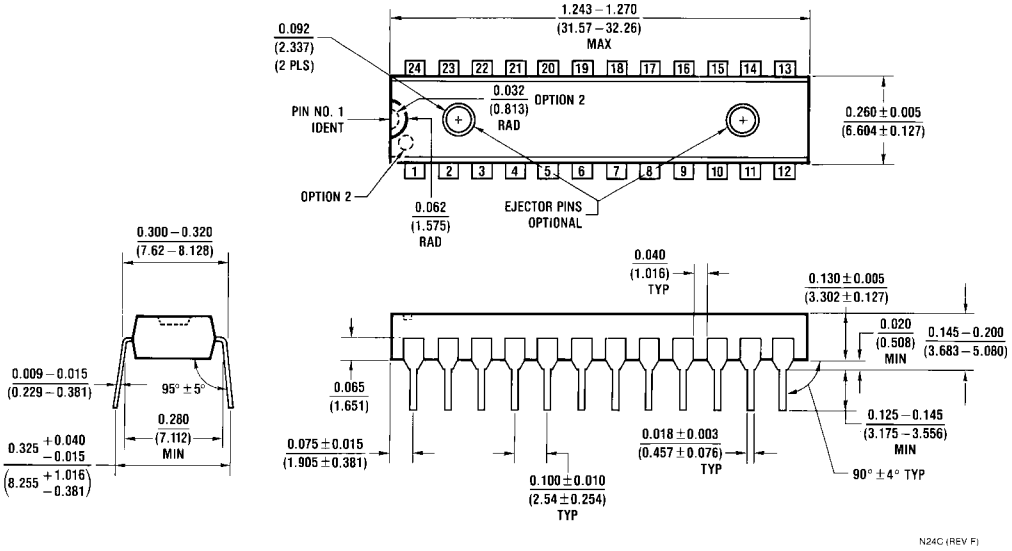
24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

March 1993
Revised November 1999

74ACTQ74
Quiet Series Dual D-Type Positive Edge-Triggered Flip-Flop

General Description

The 74ACTQ74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. Clock triggering occurs at a voltage level of the clock pulse and is not directly related to the transition time of the positive-going pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

The ACTQ74 utilizes Fairchild Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

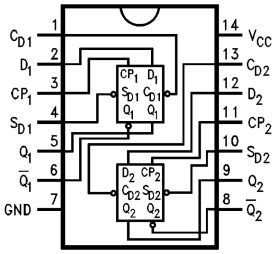
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- 4 kV minimum ESD immunity
- TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ74SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74ACTQ74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ACTQ74PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering form.

Connection Diagram



Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

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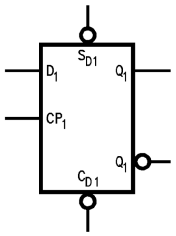
Truth Table

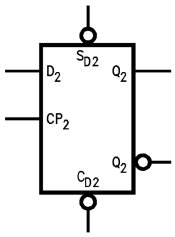
(Each Half)

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	⌐	H	H	L
H	H	⌐	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

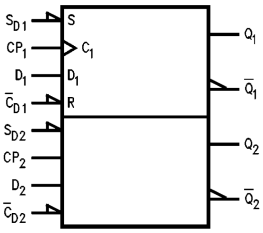
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
$Q_0(\overline{Q}_0)$ = Previous Q($\overline{Q}$) before LOW-to-HIGH Transition of Clock

Logic Symbols

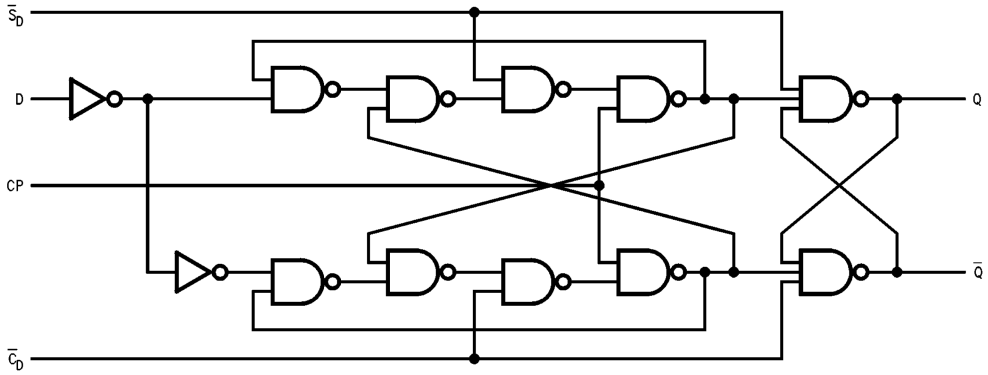




IEEE/IEC



Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J) PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 2)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: PDIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n − 1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	5.0	145	200		125		MHz
t_{PLH} t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	5.0	3.0	7.0	8.5	3.0	9.0	ns
t_{PLH} t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	5.0	3.0	6.5	8.0	3.0	8.6	ns
t_{OSLH} t_{OSHL}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP_n	5.0	1.0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to CP_n	5.0	−0.5	1.5	1.5	ns
t_W	CP_n or $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ Pulse Width	5.0	3.0	4.0	4.0	ns
t_{REC}	Recovery Time $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP	5.0	−2.5	1.5	1.5	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	60.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

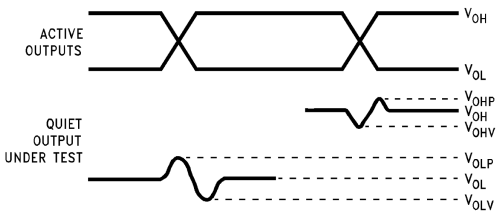
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

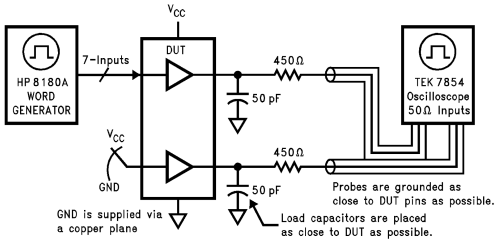
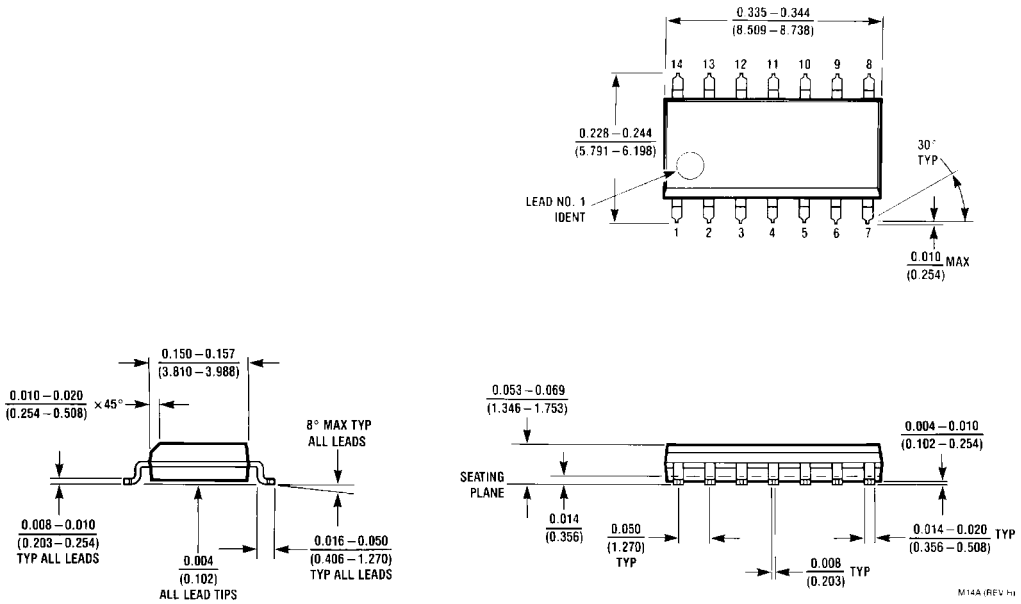


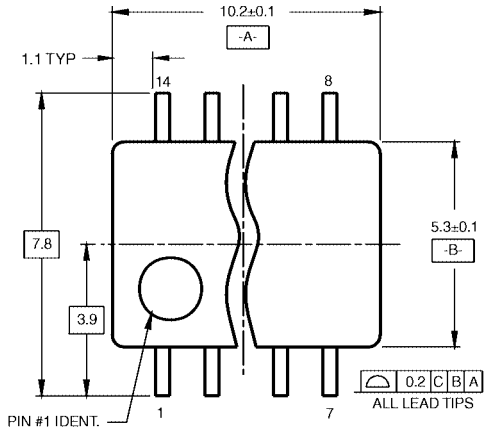
FIGURE 2. Simultaneous Switching Test Circuit

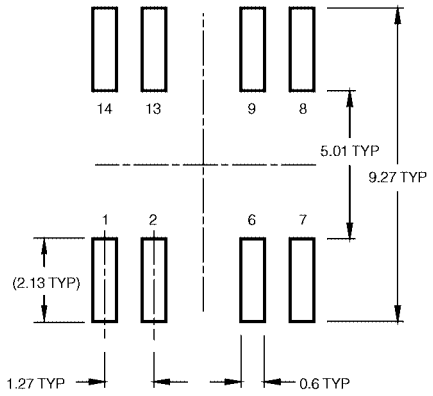
Physical Dimensions inches (millimeters) unless otherwise noted



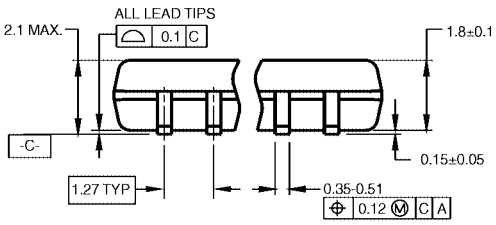
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

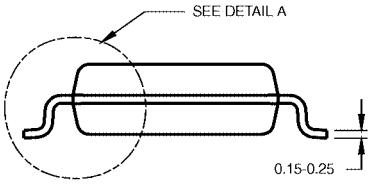
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



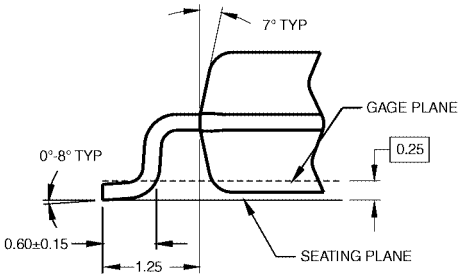


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

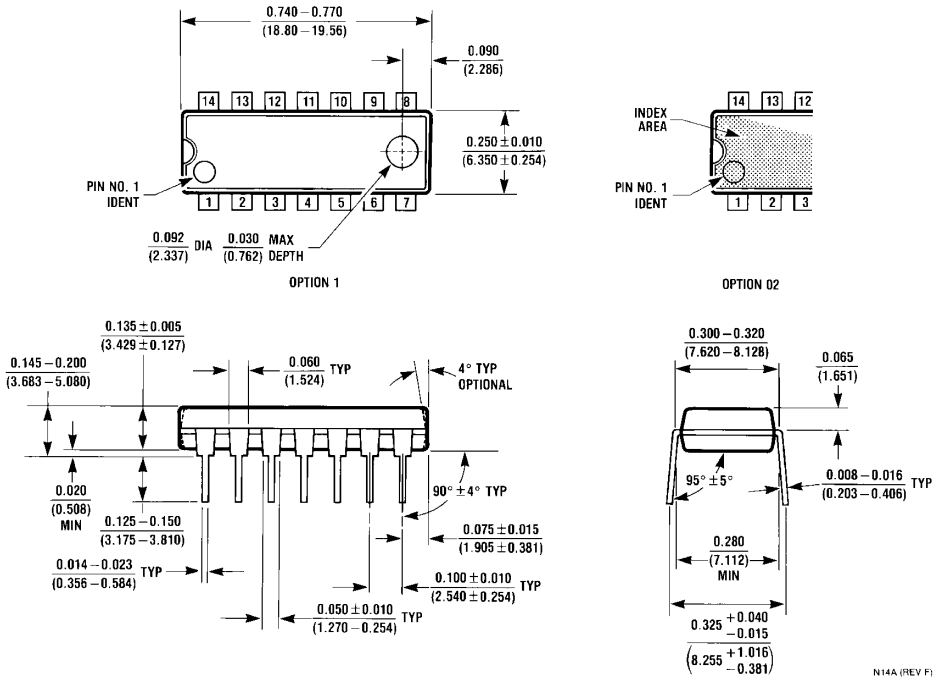
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

March 1990
Revised November 1998

74ACTQ821
Quiet Series™ 10-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACTQ821 is a 10-bit D-type flip-flop with non-inverting 3-STATE outputs arranged in a broadside pinout. The ACTQ821 utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

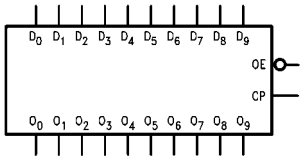
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Non-inverting 3-STATE outputs for bus interfacing
- 4 kV minimum ESD immunity
- Outputs source/sink 24 mA
- Functionally identical to the AM29821

Ordering Code:

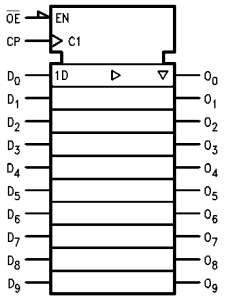
Order Number	Package Number	Package Description
74ACTQ821SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ821SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols

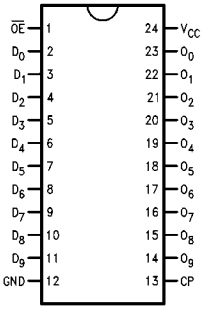


IEEE/IEC



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
D_0–D_9	Data Inputs
O_0–O_9	Data Outputs
$\overline{OE}$	Output Enable Input
CP	Clock Input

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Functional Description

The ACTQ821 consists of ten-bit D-type edge-triggered flip-flops. The buffered Clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW the contents of the flip-flops are available at the outputs. When $\overline{OE}$ is HIGH the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

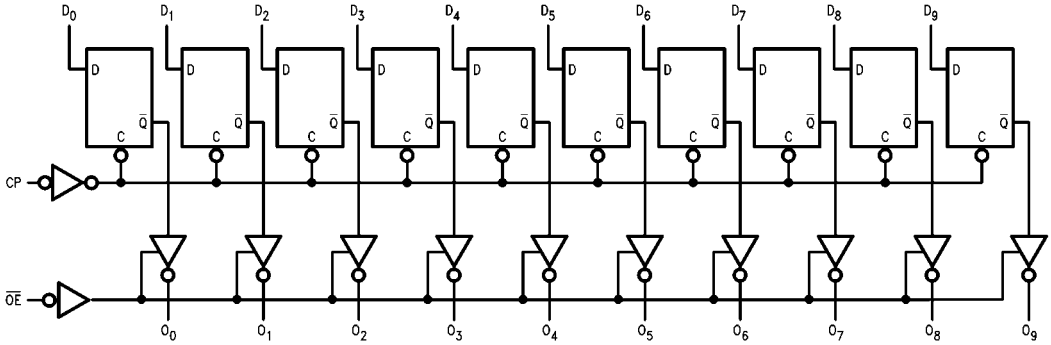
The ACTQ821 is functionally and pin compatible with the AM29821.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	⌐	L	L	Z	High Z
H	⌐	H	H	Z	High Z
L	⌐	L	L	L	Load
L	⌐	H	H	H	Load

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	− 0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	− 20 mA
V_I = V_{CC} + 0.5V	+ 20 mA
DC Input Voltage (V_I)	− 0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = − 0.5V	− 20 mA
V_O = V_{CC} + 0.5V	+ 20 mA
DC Output Voltage (V_O)	− 0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	− 65°C to + 150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	− 40°C to + 85°C
Minimum Input Edge Rate ΔV/Δt	
Minimum Input Edge Rate ΔV/Δt	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = + 25°C	T_A = − 40°C to + 85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum Low Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum High Level	4.5	4.49	4.4	4.4	V	I_{OUT} = − 50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
						V	V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = − 24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum Low Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE	5.5		±0.5	±5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	− 0.6	− 1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum High Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

DC Electrical Characteristics (Continued)

Note 6: Maximum number of data inputs (n) switching. (n–1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	5.0	120			110		MHz
t_{PLH} t_{PHL}	Propagation Delay CP to O_n	5.0	3.0	6.5	9.5	2.5	10.5	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	3.0	7.5	10.5	2.5	11.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.0	6.5	8.5	1.0	9.0	ns
t_{OSLH} t_{OSHL}	Output to Output Skew CP to O_n (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to CP	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0		1.5	1.5	ns
t_H	CP Pulse Width HIGH or LOW	5.0		4.5	5.5	ns

Note 9: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	55.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

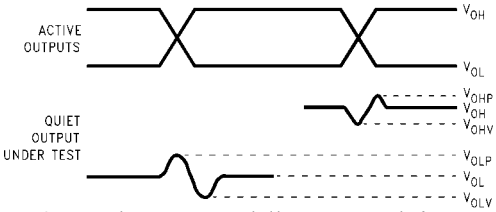
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 10: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 11: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level V_{IH} until the output begins to oscillate or steps out a min of 2ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

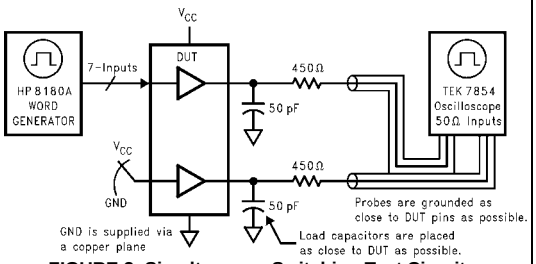
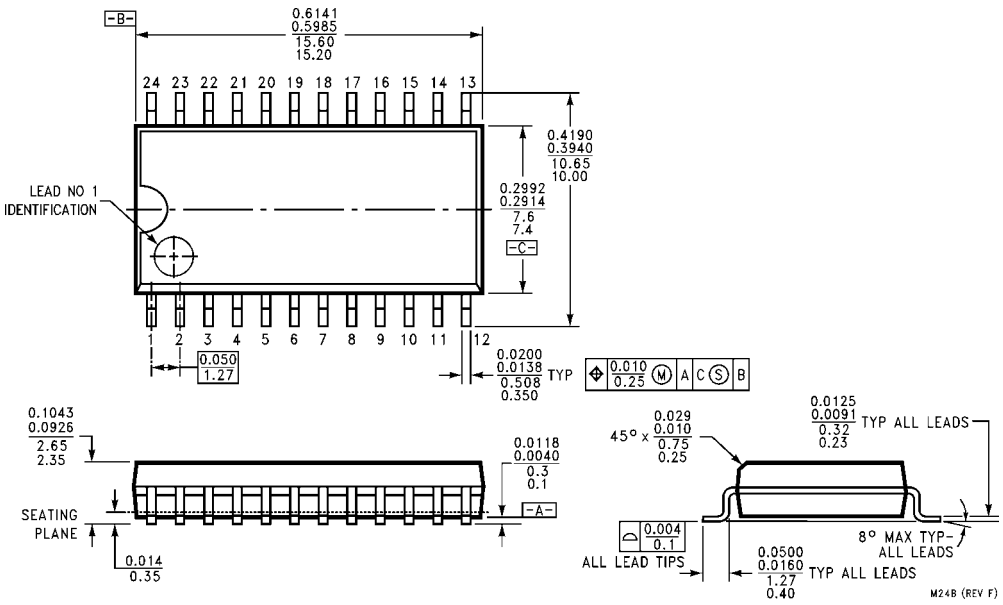


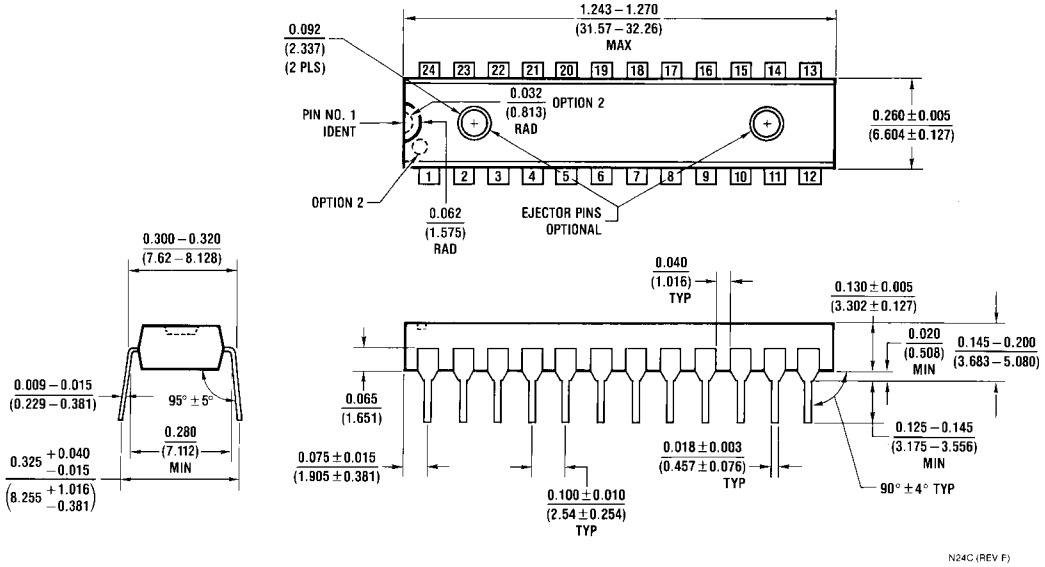
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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FAIRCHILD SEMICONDUCTOR™

May 1991
Revised December 1998

74ACTQ823
Quiet Series™ 9-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACTQ823 is a 9-bit buffered register. It features Clock Enable and Clear which are ideal for parity bus interfacing in high performance microprogramming systems. The ACTQ823 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

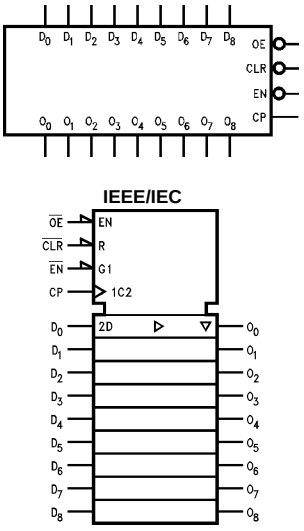
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Improved latch-up immunity
- Has TTL-compatible inputs

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ823SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ823SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

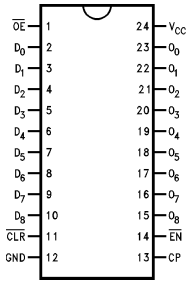
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering form.

Logic Symbols



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
D_0–D_8	Data Inputs
O_0–O_8	Data Outputs
$\overline{OE}$	Output Enable
$\overline{CLR}$	Clear
CP	Clock Input
$\overline{EN}$	Clock Enable

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

The ACTQ823 consists of nine D-type edge-triggered flip-flops. These have 3-STATE outputs for bus systems organized with inputs and outputs on opposite sides. The buffered clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops. In addition to the Clock and Output Enable pins, there are Clear ($\overline{CLR}$) and Clock Enable ($\overline{EN}$) pins. These devices are ideal for parity bus interfacing in high performance systems.

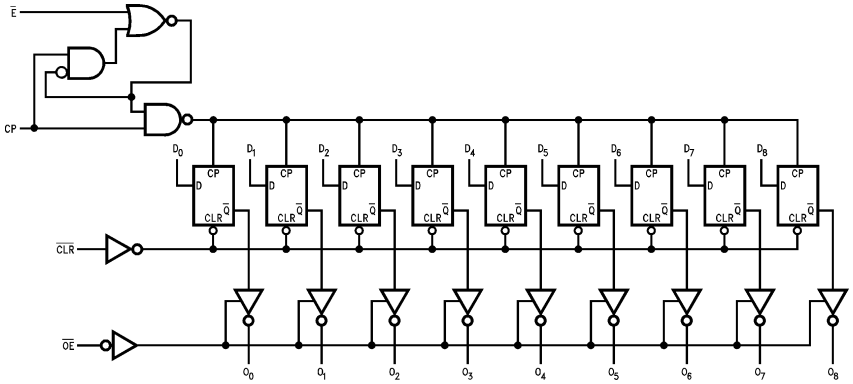
When $\overline{CLR}$ is LOW and $\overline{OE}$ is LOW, the outputs are LOW. When $\overline{CLR}$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}$ is HIGH, the outputs do not change state, regardless of the data or clock input transitions.

Function Table

Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	D	Q	O	
H	X	L	⌐	L	L	Z	High Z
H	X	L	⌐	H	H	Z	High Z
H	L	X	X	X	L	Z	Clear
L	L	X	X	X	L	L	Clear
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	H	L	⌐	L	L	Z	Load
H	H	L	⌐	H	H	Z	Load
L	H	L	⌐	L	L	L	Load
L	H	L	⌐	H	H	H	Load

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source	
or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V_{CC} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
		5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH}
	Leakage Current						V_O = V_{CC}, GND
$_{CCT}$	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
$_{OLD}$	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 2)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output	5.0	1.1	1.5		V	Figure 1, Figure 2
	Maximum Dynamic V_{OL}						(Note 5)(Note 6)
V_{OLV}	Quiet Output	5.0	−0.6	−1.2		V	Figure 1, Figure 2
	Minimum Dynamic V_{OL}						(Note 5)(Note 6)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 5)(Note 7)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 5)(Note 7)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: PDIP package.

Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

DC Electrical Characteristics for ACTQ (Continued)

Note 7: Max number of data inputs (n) switching. (n – 1) inputs switching 0V to 3V Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 8)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay CP to O_n	5.0	2.0	7.0	9.0	2.0	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay CLR to O_n	5.0	2.0	7.0	9.0	2.0	10.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	8.0	10.0	2.5	11.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.0	6.0	8.0	1.0	9.0	ns
t_{OSLH} t_{OSHL}	Output to Output Skew D_n to O_n (Note 9)	5.0		0.5	1.0		1.0	ns

Note 8: Voltage Range 5.0 is 5.0V ±0.5V.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 10)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D to CP	5.0	0.5	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to CP	5.0	0	1.5	1.5	ns
t_S	Setup Time, HIGH or LOW $\overline{EN}$ to CP	5.0	0	3.0	3.0	ns
t_H	Hold Time, HIGH or LOW $\overline{EN}$ to CP	5.0	0	1.5	1.5	ns
t_W	CP Pulse Width HIGH or LOW	5.0	2.5	4.0	4.0	ns
t_W	$\overline{CLR}$ Pulse Width, LOW	5.0	3.0	4.0		ns
t_{rec}	$\overline{CLR}$ to CP Recovery Time	5.0	1.5	3.5	4.0	ns

Note 10: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	54	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

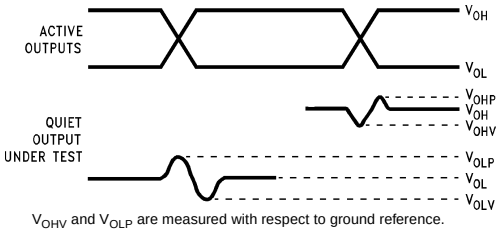
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

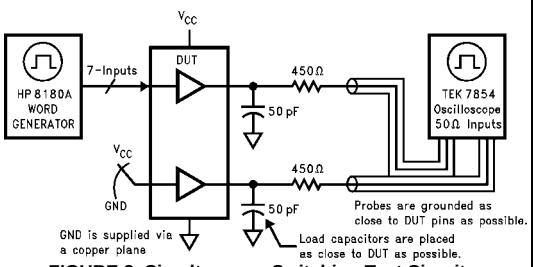
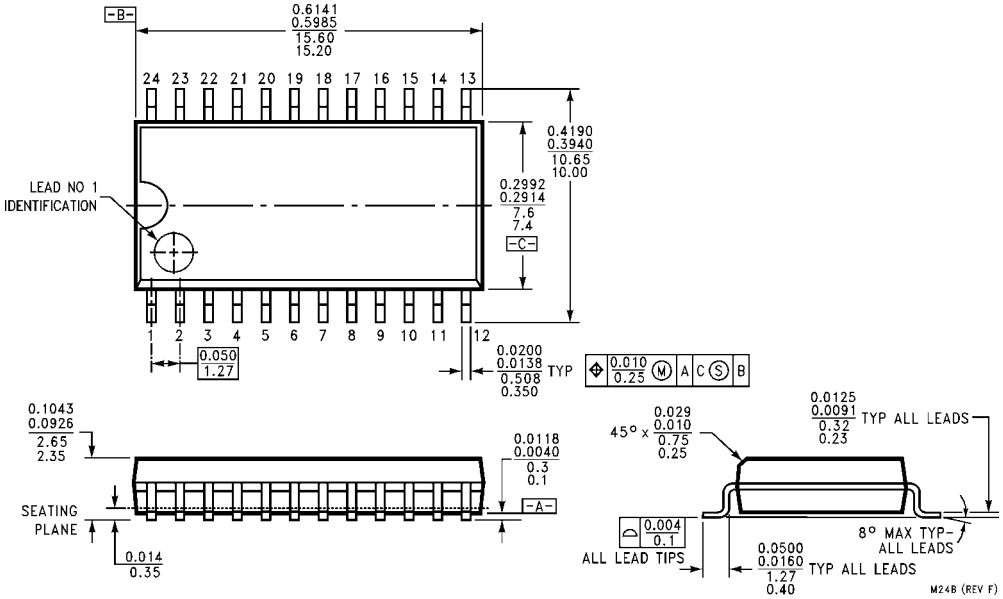


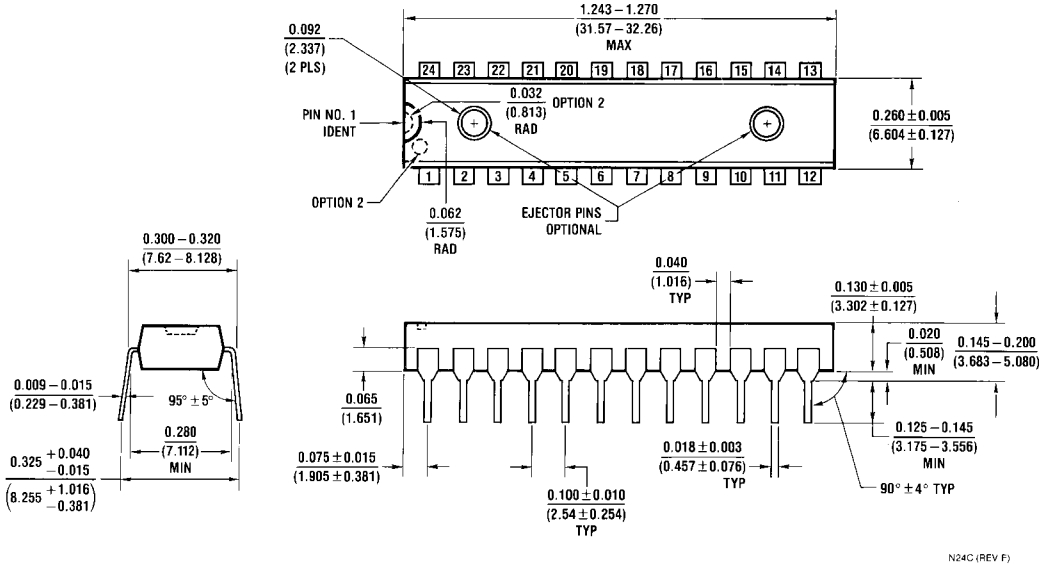
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1990
Revised December 1998

74ACTQ827
Quiet Series™ 10-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The ACTQ827 10-bit bus buffer provides high performance bus interface buffering for wide data/address paths or buses carrying parity. The 10-bit buffers have NOR output enables for maximum control flexibility. The ACTQ827 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

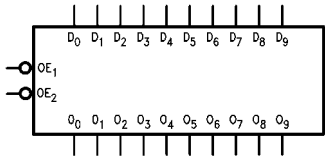
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Improved latch-up immunity
- Outputs source/sink 24 mA
- Functionally and pin-compatible to AMD's AM29827
- Has TTL-compatible inputs

Ordering Code:

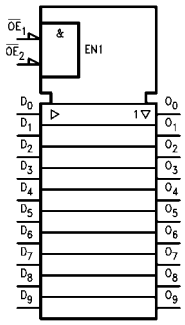
Order Number	Package Number	Package Description
74ACTQ827SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ827SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols

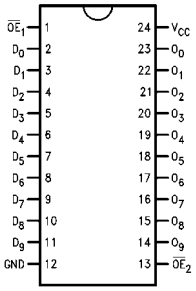


IEEE/IEC



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable
D_0–D_9	Data Inputs
O_0–O_9	Data Outputs

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

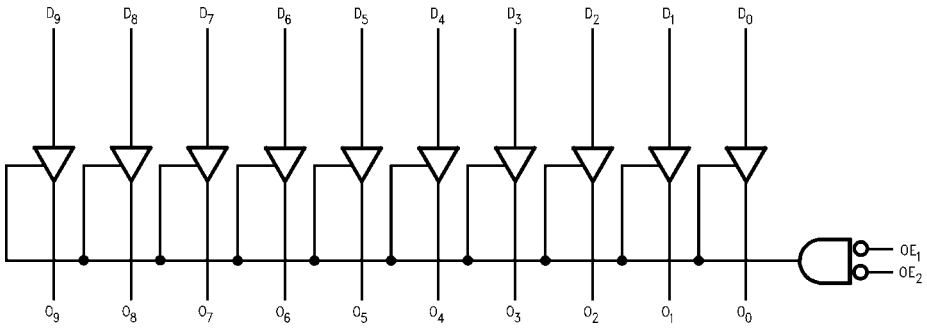
The ACTQ827 line driver is designed to be employed as memory address driver, clock driver and bus-oriented transmitter/receiver. The devices have 3-STATE outputs controlled by the Output Enable ($\overline{OE}$) pins. When the $\overline{OE}$ is LOW, the device is transparent. When $\overline{OE}$ is HIGH, the device is in 3-STATE mode.

Function Table

Inputs		Outputs	Function
$\overline{OE}$	D_n	O_n	
L	H	H	Transparent
L	L	L	Transparent
H	X	Z	High Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source	
or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristic

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	I_{OUT} = −50 µA
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 µA
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Current	5.5		±0.5	±5.0	µA	$V_I = V_{IL}$, V_{IH} $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC}$ − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.6V		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.3		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.0		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

DC Electrical Characteristic (Continued)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n–1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold. (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay Data to Output	5.0	2.5	5.6	8.0	2.5	9.0	ns
t_{PZL} t_{PZH}	Output Enable Time	5.0	3.0	7.1	10.0	3.0	11.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time	5.0	1.0	5.8	8.0	1.0	8.5	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 8) Data to Output	5.0		0.5	1.5		1.5	ns

Note 7: Voltage Range 5.0 is 5.0V ±0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	82	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

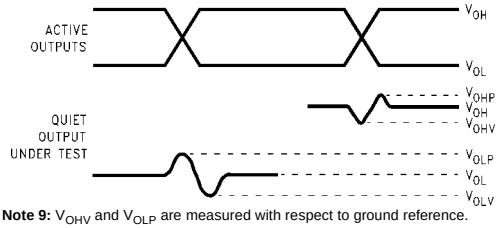
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the word generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note 9: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 10: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

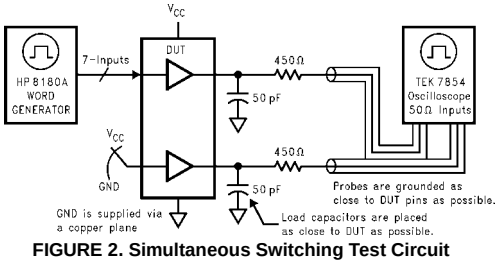
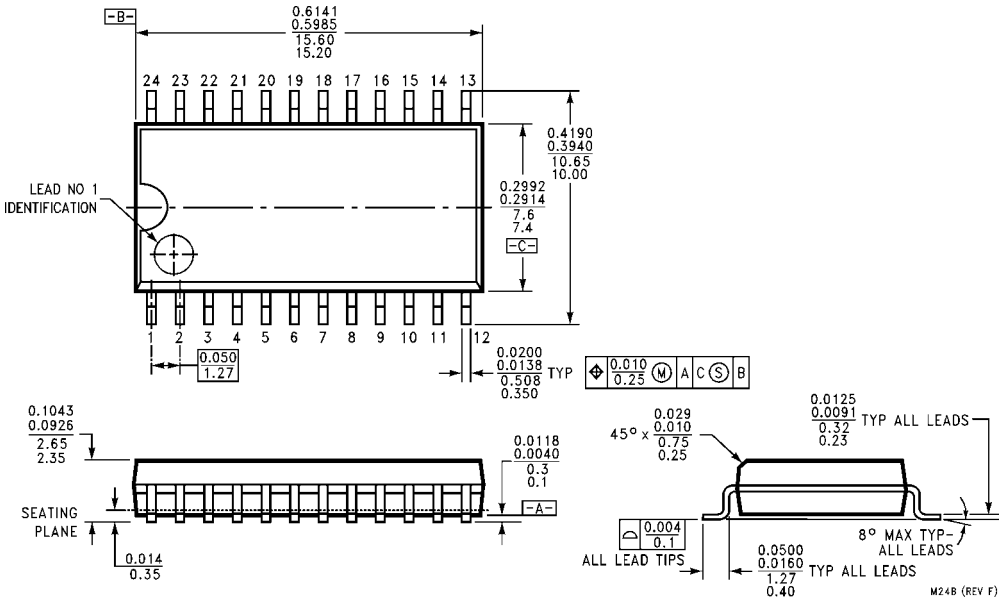


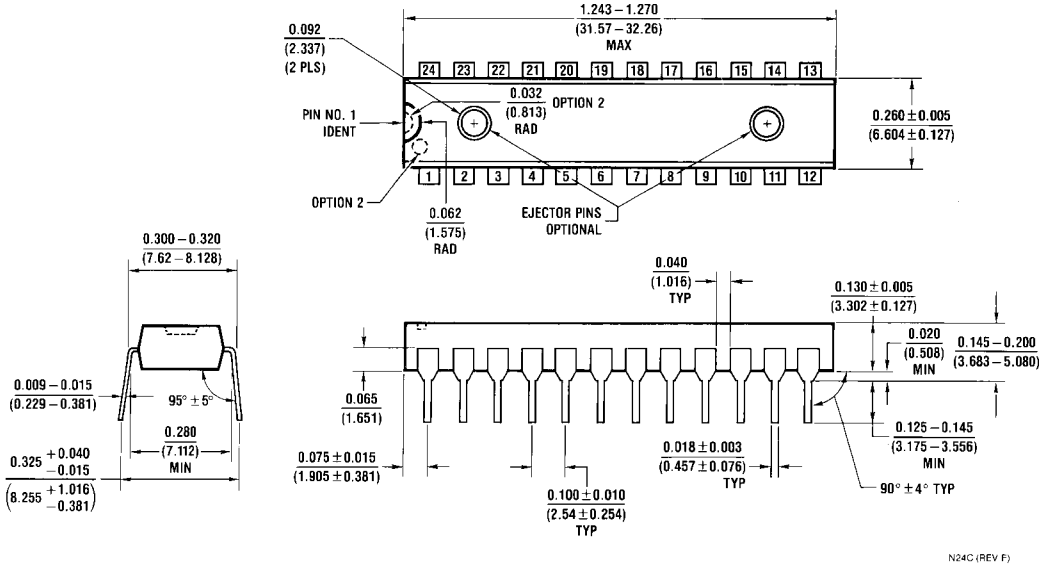
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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FAIRCHILD SEMICONDUCTOR™

March 1990
Revised November 1998

74ACTQ841
Quiet Series™ 10-Bit Transparent Latch with 3-STATE Outputs

General Description

The ACTQ841 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths or buses carrying parity. The 841 is a 10-bit transparent latch, a 10-bit version of the 373. The ACTQ841 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

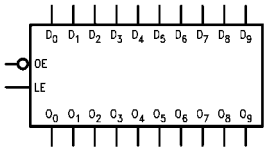
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Improved latch-up immunity
- Outputs source/sink 24 mA
- Has TTL-compatible inputs

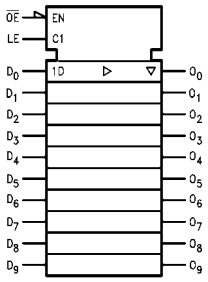
Ordering Code:

Order Number	Package Number	Package Description
74ACTQ841SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ841SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC, MS-100, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

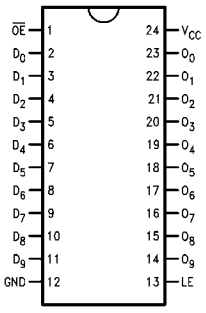
Logic Symbols





Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
D_0–D_9	Data Inputs
O_0–O_9	3-STATE Outputs
$\overline{OE}$	Output Enable
LE	Latch Enable

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

The ACTQ841 consists of ten D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition.

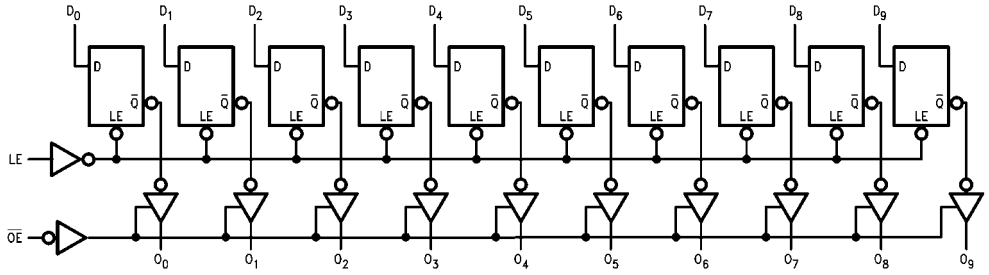
On the LE HIGH-to-LOW transition, the data that meets the setup and hold time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

Function Table

Inputs			Internal	Output	Function
$\overline{OE}$	LE	D	Q	O	
X	X	X	X	Z	High Z
H	H	L	L	Z	High Z
H	H	H	H	Z	High Z
H	L	X	NC	Z	Latched
L	H	L	L	L	Transparent
L	H	H	H	H	Transparent
L	L	X	NC	NC	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	− 0.5V to + 7.0V
DC Input Diode Current (I_{IK})	
V_I = − 0.5V	− 20 mA
V_I = V_{CC} + 0.5V	+ 20 mA
DC Input Voltage (V_I)	− 0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = − 0.5V	− 20 mA
V_O = V_{CC} + 0.5V	+ 20 mA
DC Output Voltage (V_O)	− 0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	− 65°C to + 150°C
DC Latch-Up Source or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	− 40°C to + 85°C
Minimum Input Edge Rate ΔV/Δt	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = − 40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level	4.5	1.5	2.0	2.0	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum Low Level	4.5	1.5	0.8	0.8	V	V_{OUT} = 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum High Level	4.5	4.49	4.4	4.4	V	I_{OUT} = − 50 μA
	Output Voltage	5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		4.5		3.86	3.76	V	I_{OH} = − 24 mA
		5.5		4.86	4.76		I_{OH} = − 24 mA (Note 2)
V_{OL}	Maximum Low Level	4.5	0.001	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		4.5		0.36	0.44	V	I_{OL} = − 24 mA
		5.5		0.36	0.44		I_{OL} = − 24 mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum High Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Note 4)(Note 6)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

DC Electrical Characteristics (Continued)

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: PDIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n – 1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay D_n to O_n	5.0	2.5	7.0	9.5	2.0	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay LE to O_n	5.0	2.5	7.0	9.5	2.0	10.0	ns
t_{PZH} t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	8.5	11.0	2.0	12.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.0	6.0	9.0	1.0	9.5	ns
t_{OSLH} t_{OSHL}	Output to Output Skew D_n to O_n (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0		1.5	1.5	ns
t_W	LE Pulse Width, HIGH	5.0		4.0	4.0	ns

Note 9: Voltage Range 5.0 is 5.0V ±0.5V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	85.0	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

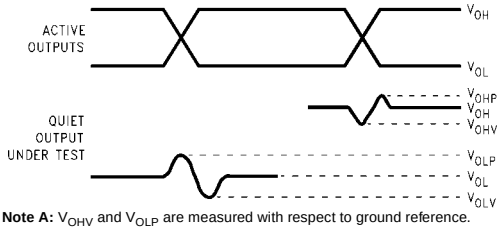
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.



Note A: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note B: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out of a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

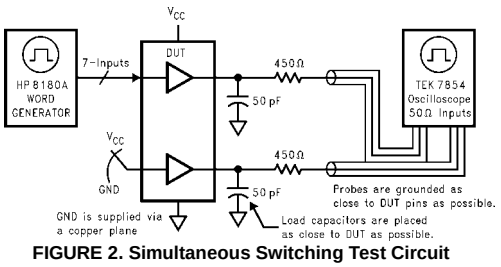
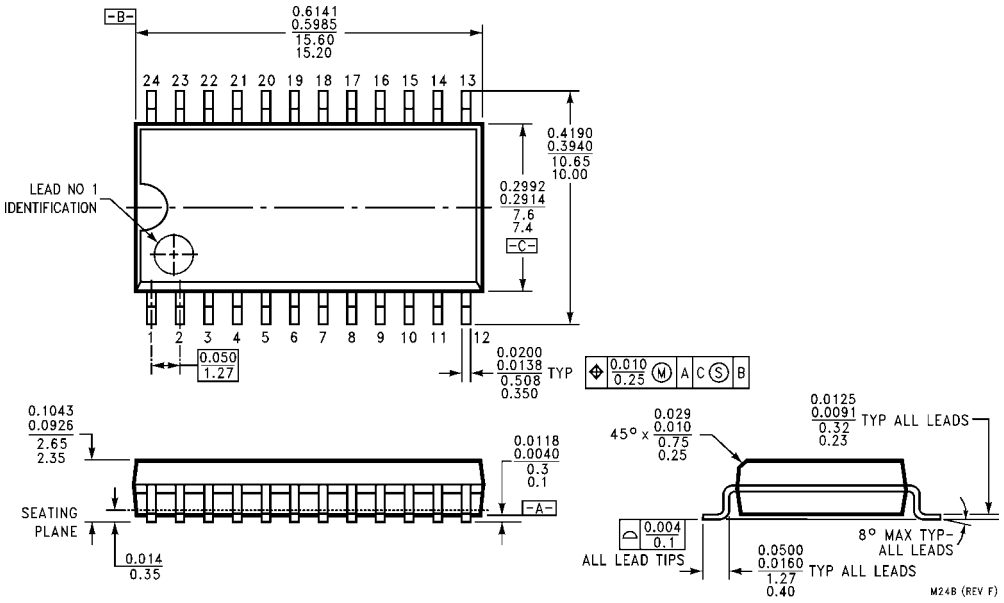


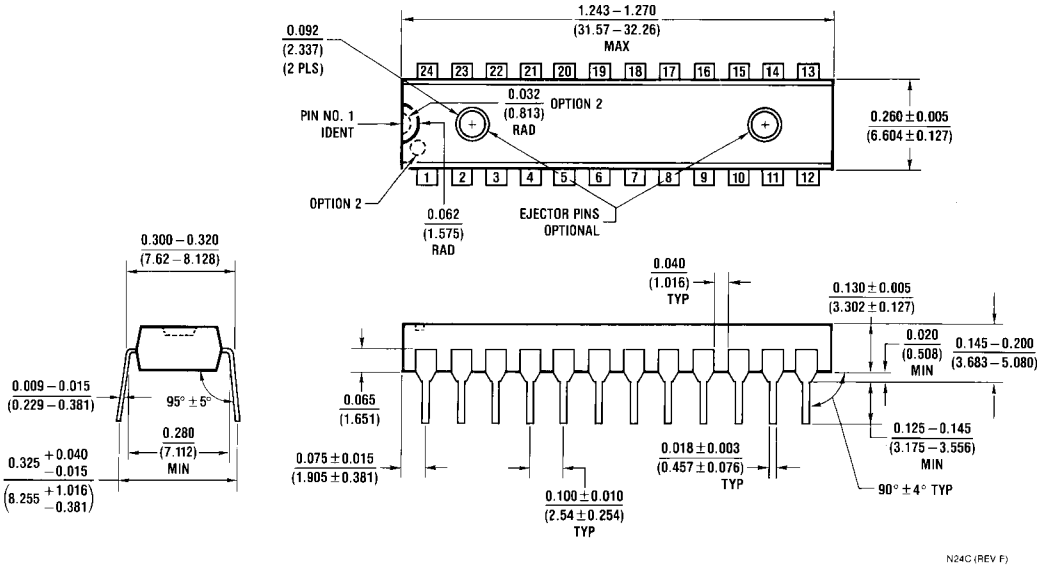
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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FAIRCHILD SEMICONDUCTOR™

March 1990
Revised December 1998

74ACTQ843
Quiet Series™ 9-Bit Transparent Latch with 3-STATE Outputs

General Description

The ACTQ843 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths. The ACTQ843 utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

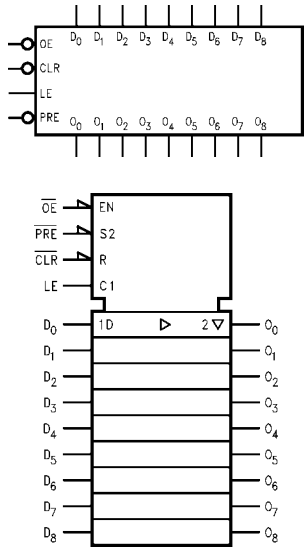
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of package for easy interface with microprocessors
- Improved latch-up immunity
- Outputs source/sink 24 mA
- ACTQ843 has TTL-compatible inputs
- Functionally and pin-compatible to AMD's AM29843
- 3-STATE outputs for bus interfacing

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ843SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ACTQ843SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide

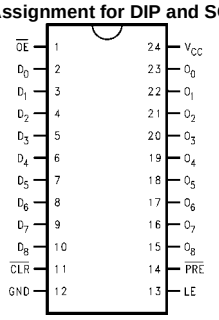
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram

Pin Assignment for DIP and SOIC



Pin Descriptions

Pin Names	Description
D_0–D_8	Data Inputs
O_0–O_8	Data Outputs
$\overline{OE}$	Output Enable
LE	Latch Enable
$\overline{CLR}$	Clear
$\overline{PRE}$	Preset

FACT™, Quiet Series™, FACT Quiet Series™ and GTO™ are trademarks of Fairchild Semiconductor Corporation.

Functional Description

The ACTQ843 consists of nine D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition. On the LE HIGH-to-LOW transition, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state.

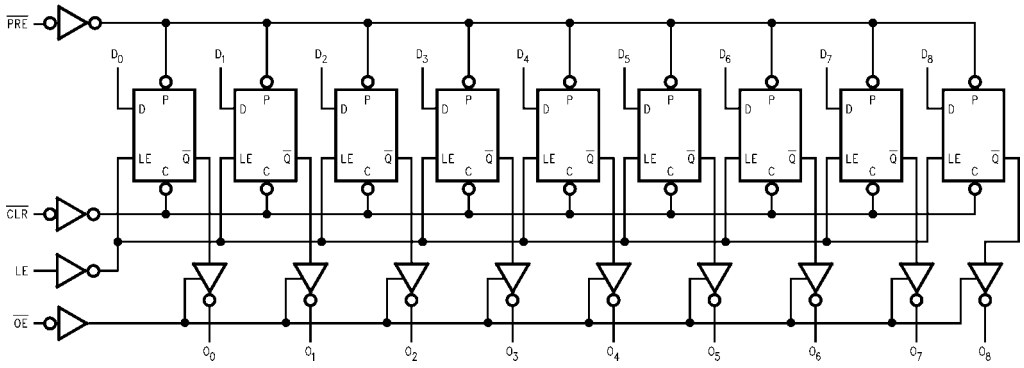
In addition to the LE and $\overline{OE}$ pins, the ACTQ843 has a Clear ($\overline{CLR}$) pin and a Preset ($\overline{PRE}$) pin. These pins are ideal for parity bus interfacing in high performance systems. When $\overline{CLR}$ is LOW, the outputs are LOW if $\overline{OE}$ is LOW. When $\overline{CLR}$ is HIGH, data can be entered into the latch. When $\overline{PRE}$ is LOW, the outputs are HIGH if $\overline{OE}$ is LOW. Preset overrides $\overline{CLR}$.

Function Table

Inputs					Internal	Outputs	Function
$\overline{CLR}$	$\overline{PRE}$	$\overline{OE}$	LE	D	Q	O	
H	H	H	H	L	L	Z	High Z
H	H	H	H	H	H	Z	High Z
H	H	H	L	X	NC	Z	Latched
H	H	L	H	L	L	L	Transparent
H	H	L	H	H	H	H	Transparent
H	H	L	L	X	NC	NC	Latched
H	L	L	X	X	H	H	Preset
L	H	L	X	X	L	L	Clear
L	L	L	X	X	H	H	Preset
L	H	H	L	X	L	Z	Clear/High Z
H	L	H	L	X	H	Z	Preset/High Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source	
or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$ Typ	$T_A = -40°C$ to $+85°C$ Guaranteed Limits		Units	Conditions
V_{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	2.0	2.0		
V_{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.5	0.8	0.8		
V_{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4	V	$I_{OUT} = -50\ \mu A$
		5.5	5.49	5.4	5.4		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		3.86	3.76	V	$I_{OH} = 24$ mA
		5.5		4.86	4.76		$I_{OH} = 24$ mA (Note 2)
V_{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		5.5	0.001	0.1	0.1		
							$V_{IN} = V_{IL}$ or V_{IH}
		4.5		0.36	0.44	V	$I_{OL} = 24$ mA
		5.5		0.36	0.44		$I_{OL} = 24$ mA (Note 2)
I_{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	µA	$V_I = V_{CC}$, GND
I_{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0	µA	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}$, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I_{OLD}	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65V$ Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	$V_{OHD} = 3.85V$ Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0	µA	$V_{IN} = V_{CC}$ or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−1.2		V	Figure 1, Figure 2 (Note 4)(Note 5)
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.0		V	(Note 4)(Note 6)
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

DC Electrical Characteristics (Continued)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n − 1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 7)	$T_A = +25°C$, $C_L = 50$ pF			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay D_n to O_n	5.0	2.5	6.2	9.5	2.0	10.0	ns
t_{PHL}	Propagation Delay D_n to O_n	5.0	2.5	6.7	9.5	2.0	10.0	ns
t_{PLH}	Propagation Delay LE to O_n	5.0	2.5	7.1	9.0	2.0	10.0	ns
t_{PHL}	Propagation Delay LE to O_n	5.0	2.5	6.9	9.0	2.0	10.0	ns
t_{PLH}	Propagation Delay $\overline{PRE}$ to O_n	5.0	2.5	7.3	10.0	2.0	11.0	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	7.2	11.0	2.0	12.0	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	7.2	9.5	2.0	10.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	7.5	9.5	2.0	10.5	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	5.0	8.0	1.0	8.5	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	5.1	8.0	1.0	8.5	ns
t_{PHL}	Propagation Delay $\overline{PRE}$ to O_n	5.0	2.5	6.7	10.0	2.0	11.0	ns
t_{PLH}	Propagation Delay $\overline{CLR}$ to O_n	5.0	2.5	7.3	11.0	2.0	12.0	ns
t_{OSLH} t_{OSHL}	Output to Output Skew (Note 8) D_n to O_n	5.0		0.5	1.5		1.5	ns

Note 7: Voltage Range 5.0 is 5.0V ±0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V) (Note 9)	$T_A = +25°C$, $C_L = 50$ pF		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW D_n to LE	5.0		3.0	3.0	ns
t_H	Hold Time, HIGH or LOW D_n to LE	5.0		1.5	1.5	ns
t_W	LE Pulse Width, HIGH	5.0		4.0	4.0	ns
t_W	$\overline{PRE}$ Pulse Width, LOW	5.0		4.0	4.0	ns
t_W	$\overline{CLR}$ Pulse Width, LOW	5.0		4.0	4.0	ns
t_{rec}	$\overline{PRE}$ Recovery Time	5.0		2.0	2.0	ns
t_{rec}	$\overline{CLR}$ Recovery Time	5.0		2.0	2.0	ns

Note 9: Voltage Range 5.0 is 5.0V ±0.5V.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	52	pF	V_{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

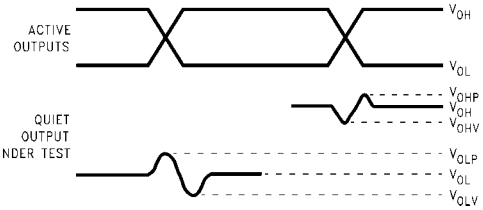


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 10: V_{OHV} and V_{OLP} are measured with respect to ground reference.

Note 11: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level on the, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

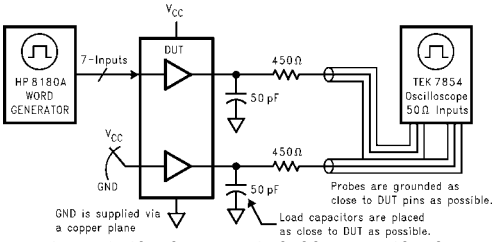
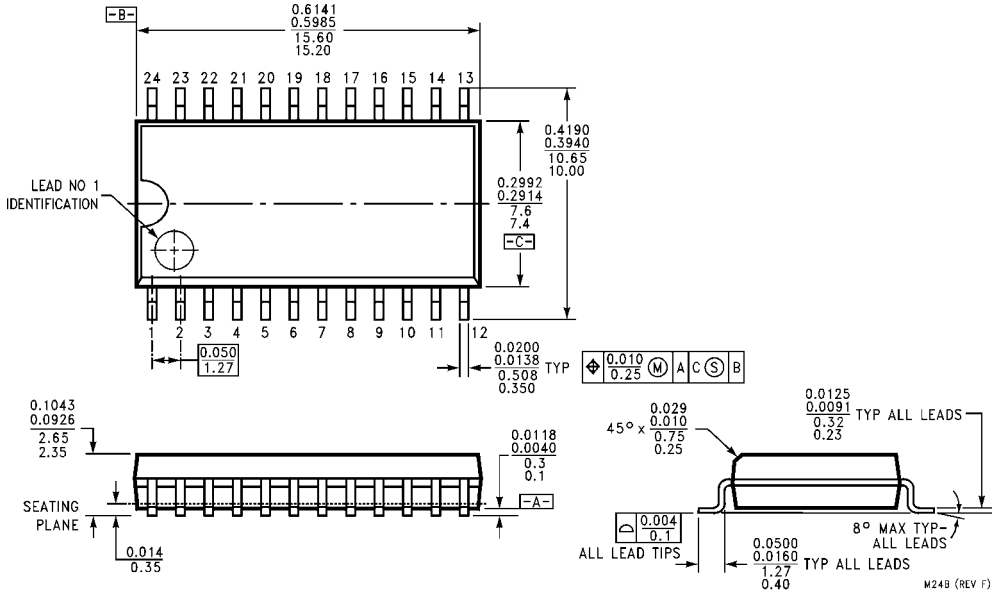


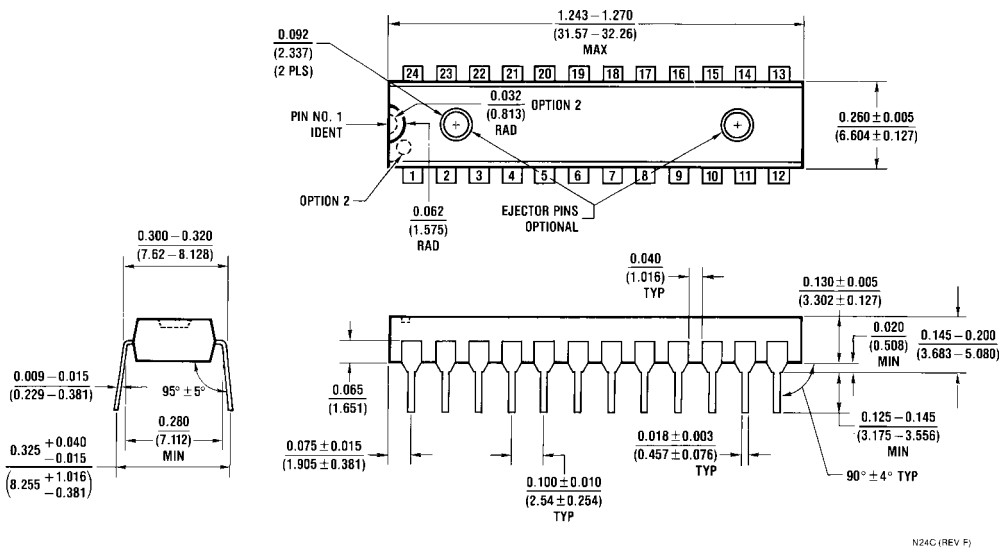
FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide Body
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300" Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1998

DM74ALS5245/74ALS5245-1 Octal 3-STATE Transceiver

General Description

This octal bus transceiver is designed for asynchronous two-way communication between data buses. The inputs include hysteresis which provides improved noise rejection. Data is transmitted either from the A bus to the B bus or from the B bus to the A bus depending on the logic level of the direction control (DIR) input. The device can be disabled via the enable input ($\overline{G}$) which causes the outputs to enter the high impedance mode so the buses are effectively isolated.

The ALS5245-1 features the same performance as the ALS5245 with the addition of increased current drive capability to meet the requirements of various bus architectures. The recommended maximum I_{OL} is increased to 48 mA.

Features

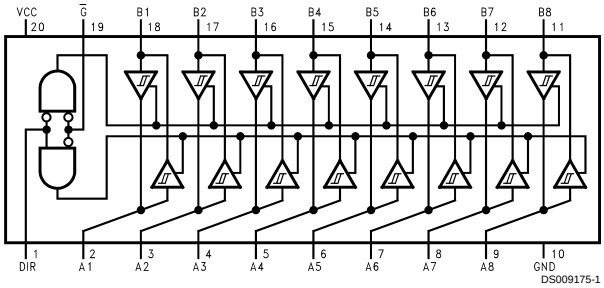
- Input Hysteresis
- Low output noise generation
- High input noise immunity
- Advanced oxide-isolated, ion implanted Schottky TTL process
- Switching specification guaranteed over the full temperature and V_{CC} range
- PNP inputs to reduce input loading
- Maximum I_{OL} is increased to 48 mA for ALS5245-1

Ordering Code:

Order Number	Package Number	Package Description
DM74ALS5245WM	M20B	20-Lead Small Outline Package – JEDEC (M)
DM74ALS5245SJ	M20D	20-Lead Small Outline Package – EIAJ (SJ)
DM74ALS5245N	N20A	20-Lead Molded Dual-in-Line Package (N)
DM74ALS5245-1WM	M20B	20-Lead Small Outline Package – JEDEC (M)
DM74ALS5245-1SJ	M20D	20-Lead Small Outline Package – EIAJ (SJ)
DM74ALS5245-1N	N20A	20-Lead Molded Dual-in-Line Package (N)

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



DS009175-1

Function Table

Control Inputs		Operation
$\overline{G}$	DIR	
L	L	B Data to A Bus
L	H	A Data to B Bus
H	X	High Impedance

L = Low Logic Level, H = High Logic Level
X = Don't Care (Either Low or High Logic Level)

Absolute Maximum Ratings (Note 1)

Supply Voltage	7V
Input Voltage	
Control Inputs	7V
I/O Ports	5.5V
Operating Free-Air Temperature Range	
DM74ALS	0˚C to +70˚C
Storage Temperature Range	−65˚C to +150˚C
Typical θ_{JA}	
N Package	56.0˚C/W
M Package	74.0˚C/W

Recommended Operating Conditions

Symbol	Parameter	DM74ALS5245		74ALS5245-1		Units
		Min	Max	Min	Max	
V_{CC}	Supply Voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High Level Input Voltage	2		2		V
V_{IL}	Low Level Input Voltage		0.8		0.8	V
I_{OH}	High Level Output Current		−15		−15	mA
I_{OL}	Low Level Output Current		24		48	mA
T_A	Free Air Operating Temperature Range	0	70	0	70	˚C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristic tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

ALS5245

Electrical Characteristics

over recommended free air temperature range. All typical values are measured at V_{CC} = 5V, T_A = 25˚C.

Symbol	Parameter	Test Conditions		DM74ALS5245			Units
				Min	Typ	Max	
V_{IK}	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA				−1.5	V
H_{YS}	Hysteresis (V_{T+} − V_{T-})	V_{CC} = Min		0.2	0.32		V
V_{OH}	High Level Output Voltage	V_{CC} = 4.5V to 5.5V	I_{OH} = −0.4 mA	V_{CC} − 2			V
		V_{CC} = Min	I_{OH} = −3 mA	2.4	3.2		
			I_{OH} = Max	2			
V_{OL}	Low Level Output Voltage	V_{CC} = Min	I_{OL} = 12 mA		0.25	0.4	V
			I_{OL} = 24 mA		0.35	0.5	
I_I	Input Current at Maximum Input Voltage	V_{CC} = Max	I/O Ports, V_I = 5.5V			100	µA
			Control Inputs, V_I = 7V			100	
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V				20	µA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−100	µA
I_O	Output Drive Current	V_{CC} = Max, V_O = 2.25V		−30		−112	mA
I_{CC}	Supply Current	V_{CC} = Max	Outputs High		30	45	mA
			Outputs Low		36	55	
			Outputs Disabled		38	58	
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	V_{CC} = 5.0V, T_A = 25˚C (*Figures 1, 2*; (Notes 2, 3))			0.5		V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	V_{CC} = 5.0V, T_A = 25˚C (*Figures 1, 2*; (Notes 2, 3))			−0.2		V
V_{IHD}	Minimum High Level Dynamic Input Voltage	V_{CC} = 5.0V, T_A = 25˚C (Notes 2, 4)			1.6		V
V_{ILD}	Maximum Low Level Dynamic Input Voltage	V_{CC} = 5.0V, T_A = 25˚C (Notes 2, 4)			1.0		V

Note 2: Plastic DIP package.

Note 3: n = number of device outputs; n−1 outputs switching, each driven 0V to 3V one output @ GND.

Note 4: n = number of device outputs; n outputs switching, n−1 inputs switching 0V to 3V. Input under test switching 3V to threshold (V_{ILD}); 0V to threshold (V_{IHD}); f = 1 MHz.

Switching Characteristics

over recommended operating free air temperature range (Note 5)

Symbol	Parameter	Conditions	From (Input) To (Output)	DM74ALS5245		Units
				Min	Max	
t_{PLH}	Propagation Delay Time Low to High Level Output	V_{CC} = 4.5V to 5.5V, $R_1 = R_2 = 500\Omega$, C_L = 50 pF	A or B to B or A	3	10	ns
t_{PHL}	Propagation Delay Time High to Low Level Output		A or B to B or A	3	10	ns
t_{PZH}	Output Enable Time to High Level Output		$\overline{G}$ to A or B	5	20	ns
t_{PZL}	Output Enable Time to Low Level Output		$\overline{G}$ to A or B	5	20	ns
t_{PHZ}	Output Disable Time from High Level Output		$\overline{G}$ to A or B	2	10	ns
t_{PLZ}	Output DisableTime from Low Level Output		$\overline{G}$ to A or B	4	15	ns

Note 5: See Section 5 for test waveforms and output load.

ALS5245-1

Electrical Characteristics

over recommended free air temperature range

Symbol	Parameter	Test Conditions		74ALS5245-1			Units
				Min	Typ	Max	
V_{IC}	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA				−1.5	V
H_{YS}	Hysteresis ($V_{T+} - V_{T-}$)	V_{CC} = Min		0.2	0.32		V
V_{OH}	High Level Output Voltage	V_{CC} = 4.5V to 5.5V	I_{OH} = −0.4 mA	V_{CC} − 2			V
		V_{CC} = Min	I_{OH} = −3 mA	2.4	3.2		
			I_{OH} = Max	2			
V_{OL}	Low Level Output Voltage	V_{CC} = Min	I_{OL} = 48 mA		0.45	0.53	V
I_I	Input Current at Maximum Input Voltage	V_{CC} = Max	I/O Ports, V_I = 5.5V			100	µA
			Control Inputs, V_I = 7V			100	
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V (Note 6)				20	µA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V (Note 6)				−100	µA
I_O	Output Drive Current	V_{CC} = Max, V_O = 2.25V		−30		−112	mA
I_{CC}	Supply Current	V_{CC} = Max	Outputs High		30	45	mA
			Outputs Low		36	55	
			Outputs Disabled		38	58	

Note 6: For I/O ports, I_{IH} and I_{IL} parameters include the 3-STATE output currents (I_{OZL} and I_{OZH}).

Switching Characteristics

over recommended operating free air temperature range (Note 7)

Symbol	Parameter	Conditions	From (Input) To (Output)	74ALS5245-1		Units
				Min	Max	
t_{PLH}	Propagation Delay Time Low to High Level Output	V_{CC} = 4.5V to 5.5V, $R_1 = R_2 = 500\Omega$, C_L = 50 pF	A or B to B or A	2	10	ns
t_{PHL}	Propagation Delay Time High to Low Level Output		A or B to B or A	3	10	ns
t_{PZH}	Output Enable Time to High Level Output		$\overline{G}$ to A or B	4	20	ns
t_{PZL}	Output Enable Time to Low Level Output		$\overline{G}$ to A or B	5	20	ns
t_{PHZ}	Output Disable Time from High Level Output		$\overline{G}$ to A or B	1	10	ns
t_{PLZ}	Output DisableTime from Low Level Output		$\overline{G}$ to A or B	3	15	ns

Note 7: See Section 5 for test waveforms and output load.

ALS Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of ALS.

Equipment:

Word Generator

Printed Circuit Board Test Fixture

Dual Trace Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the word generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. Swap out the channels that have more than 150 ps of skew until all channels being used are within 150 ps. It is important to deskew the word generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set V_{CC} to 5.0V.
5. Set the word generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.
6. Set the word generator input levels at 0V LOW and 3V HIGH. Verify levels with a digital volt meter.

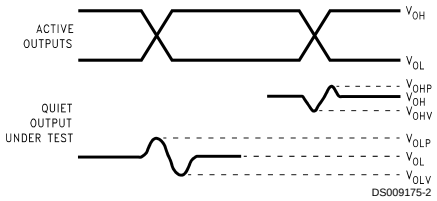


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 8: V_{OHV} and V_{OHP} are measured with respect to V_{OH} reference. V_{OLV} and V_{OLP} are measured with respect to ground reference.

Note 9: Input pulses have the following characteristics: f = 1 MHz, t_r = 3 ns, t_f = 3 ns, skew < 150 ps.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the HL transition. Measure V_{OHP} and V_{OHV} on the quiet output during the LH transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level on the word generator, V_{IH} until the output begins to oscillate. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

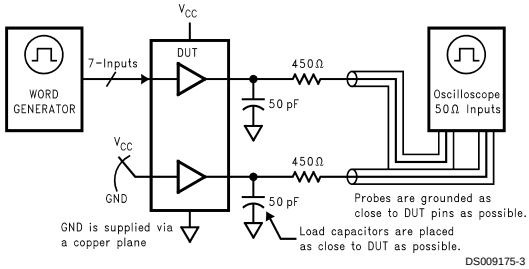
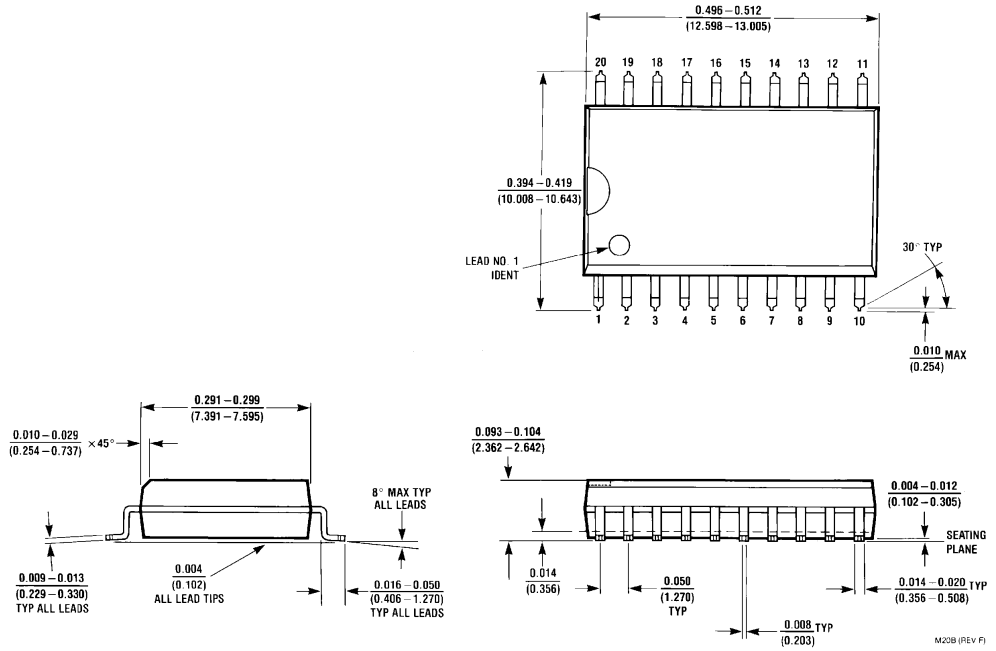
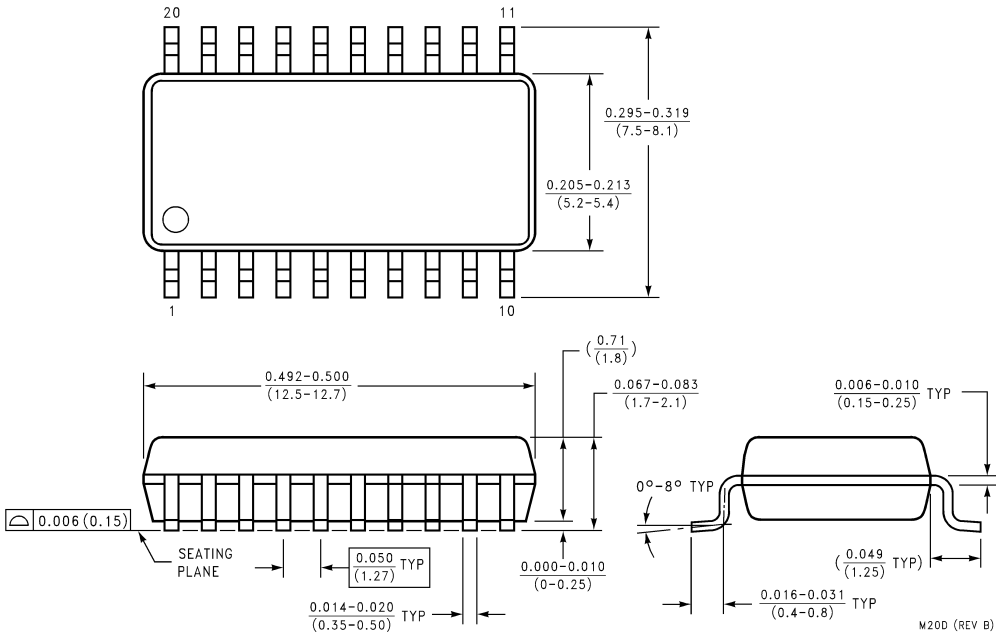


FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted

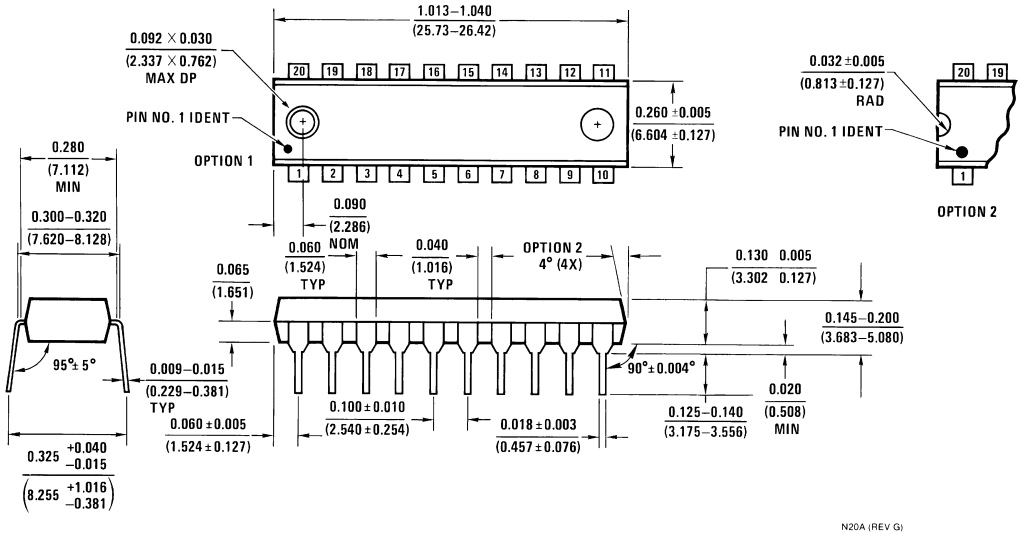


Small Outline Package-JEDEC (M)
Package Number M20B



Small Outline Package-EIAJ (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Molded Dual-In-Line Package (N)
Package Number N20A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

December 1994
Revised July 1999

74F00
Quad 2-Input NAND Gate

General Description

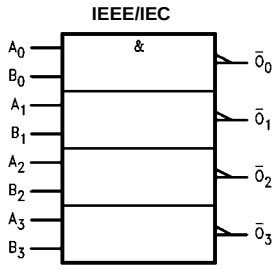
This device contains four independent gates, each of which performs the logic NAND function.

Ordering Code:

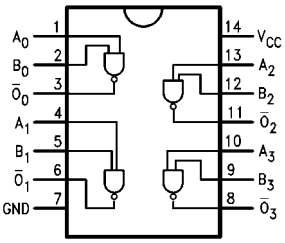
Order Number	Package Number	Package Description
74F00SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F00PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

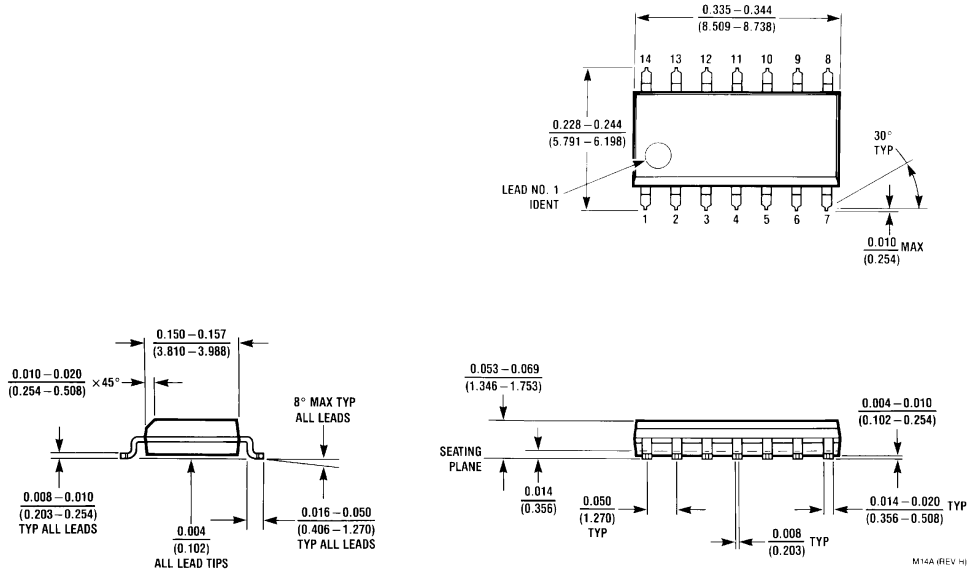
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			1.9	2.8	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			6.8	10.2	mA	Max	V_O = LOW

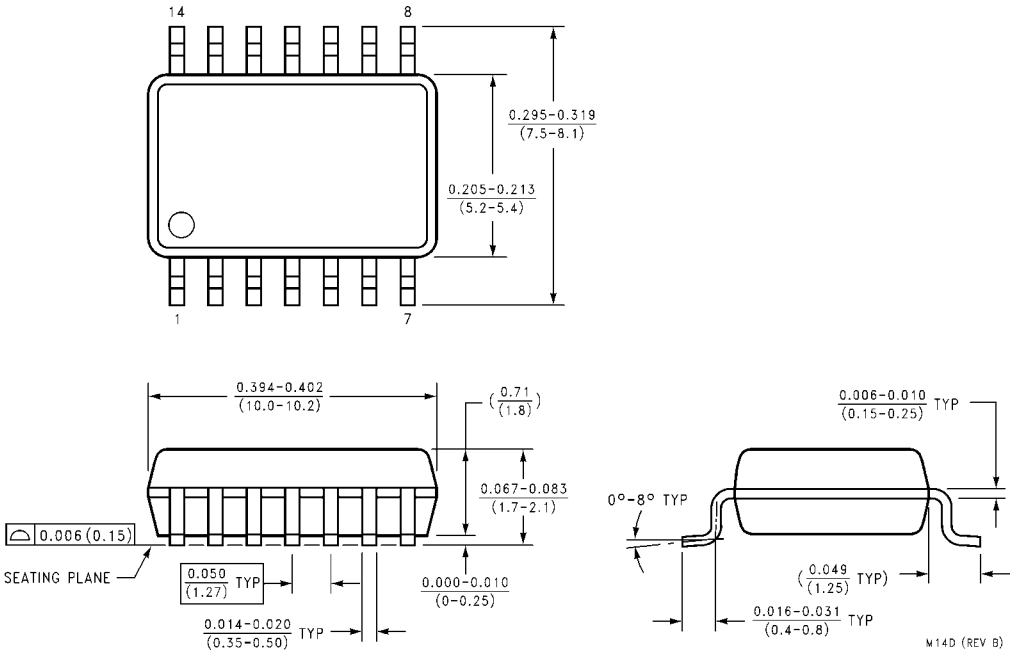
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	ns
t_{PHL}	A_n, B_n to $\overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3	

Physical Dimensions inches (millimeters) unless otherwise noted

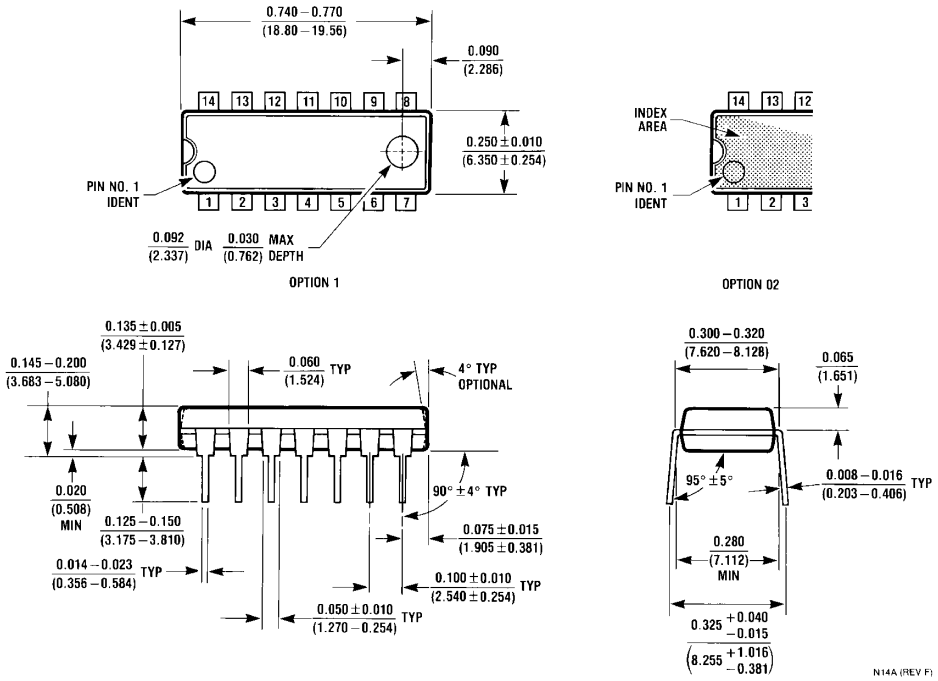


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F02
Quad 2-Input NOR Gate

General Description

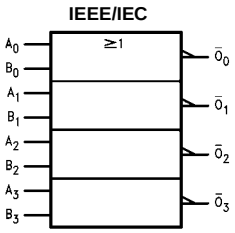
This device contains four independent gates, each of which performs the logic NOR function.

Ordering Code:

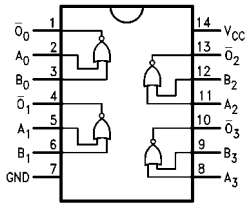
Order Number	Package Number	Package Description
74F02SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F02PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

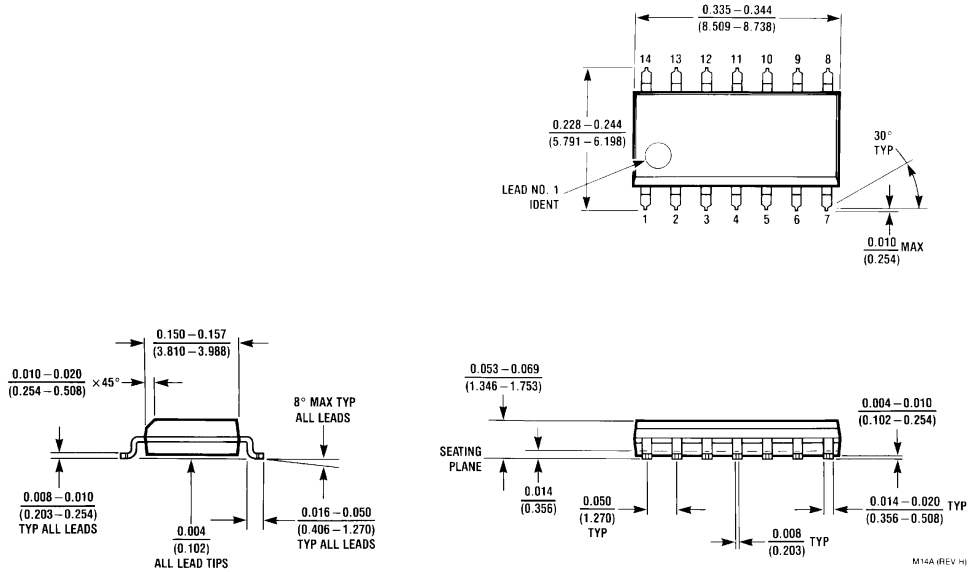
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			3.7	5.6	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			8.7	13.0	mA	Max	V_O = LOW

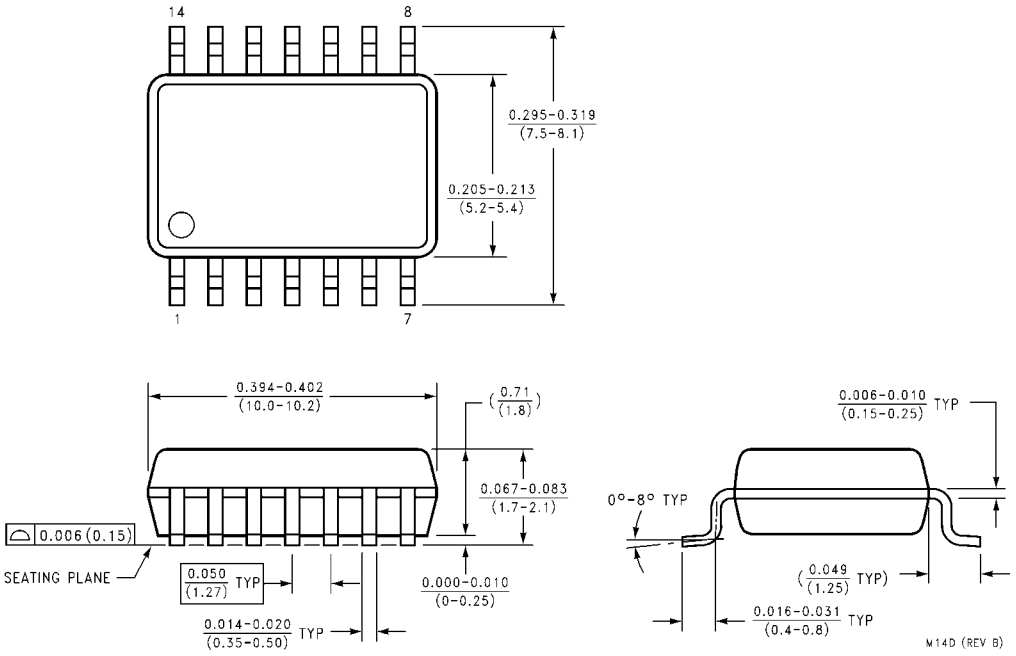
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.4	5.5	2.5	7.5	2.5	6.5	ns
t_{PHL}	A_n, B_n to $\overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3	

Physical Dimensions inches (millimeters) unless otherwise noted

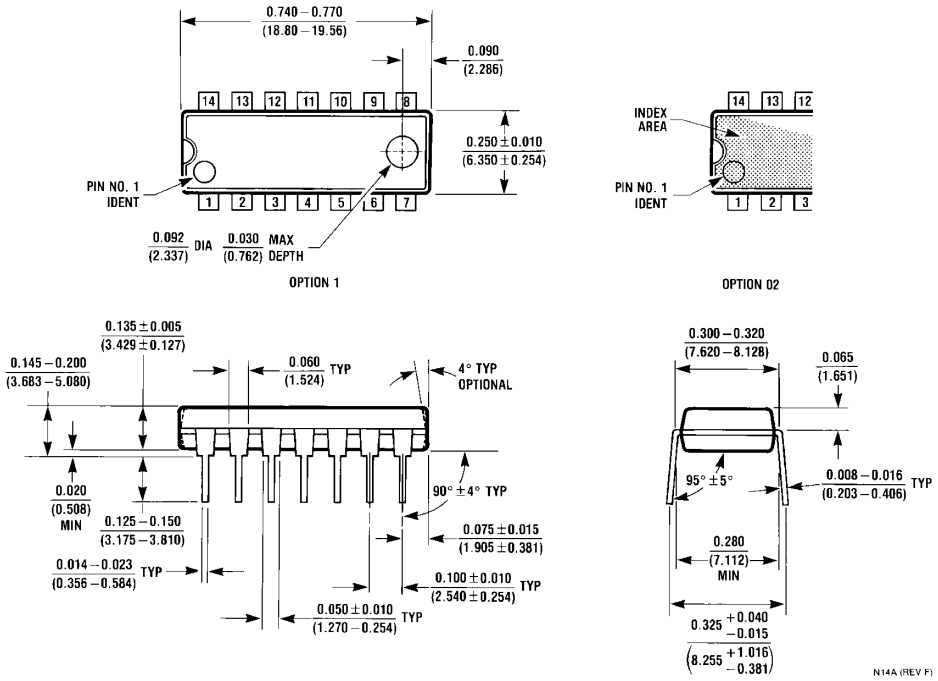


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

November 1984
Revised July 1999

74F04
Hex Inverter

General Description

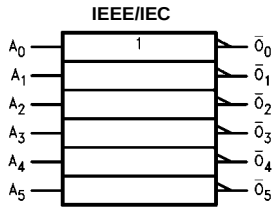
This device contains six independent gates, each of which performs the logic INVERT function.

Ordering Code:

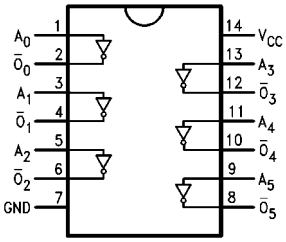
Order Number	Package Number	Package Description
74F04SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F04PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n	Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

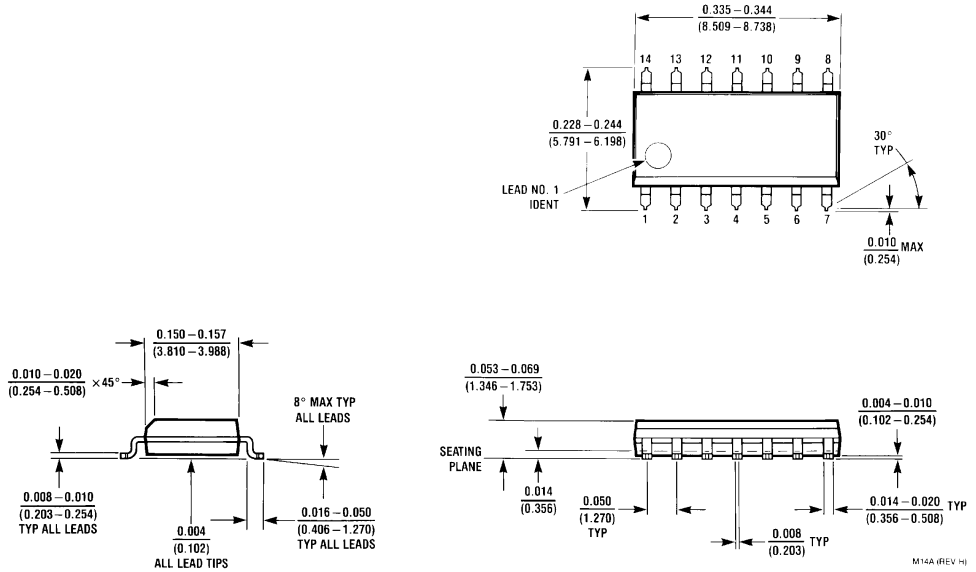
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			2.8	4.2	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			10.2	15.3	mA	Max	V_O = LOW

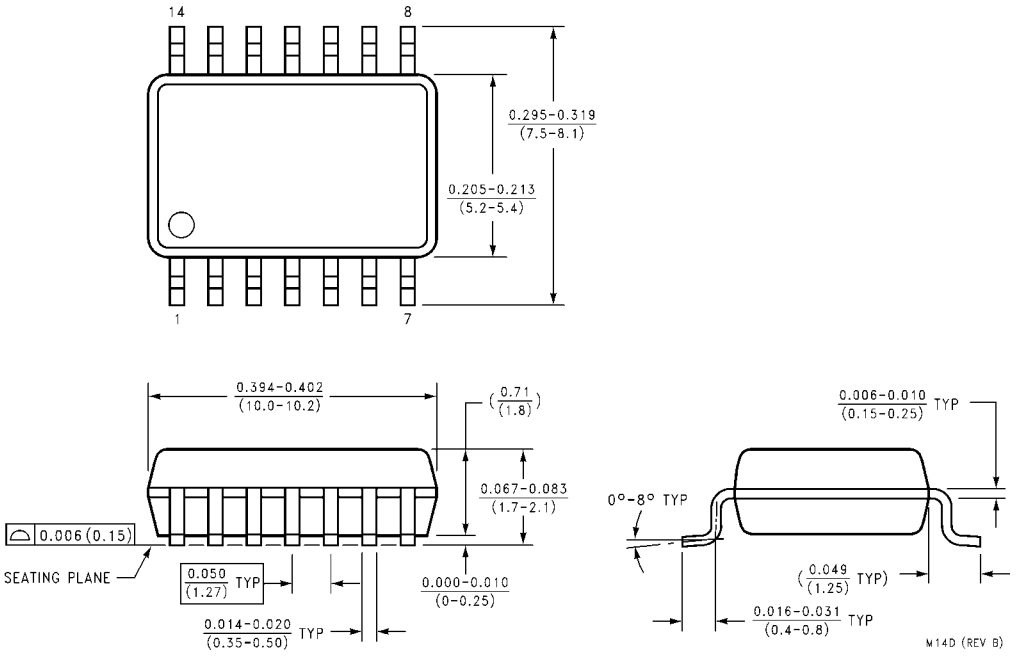
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	ns
t_{PHL}	A_n to $\overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3	

Physical Dimensions inches (millimeters) unless otherwise noted

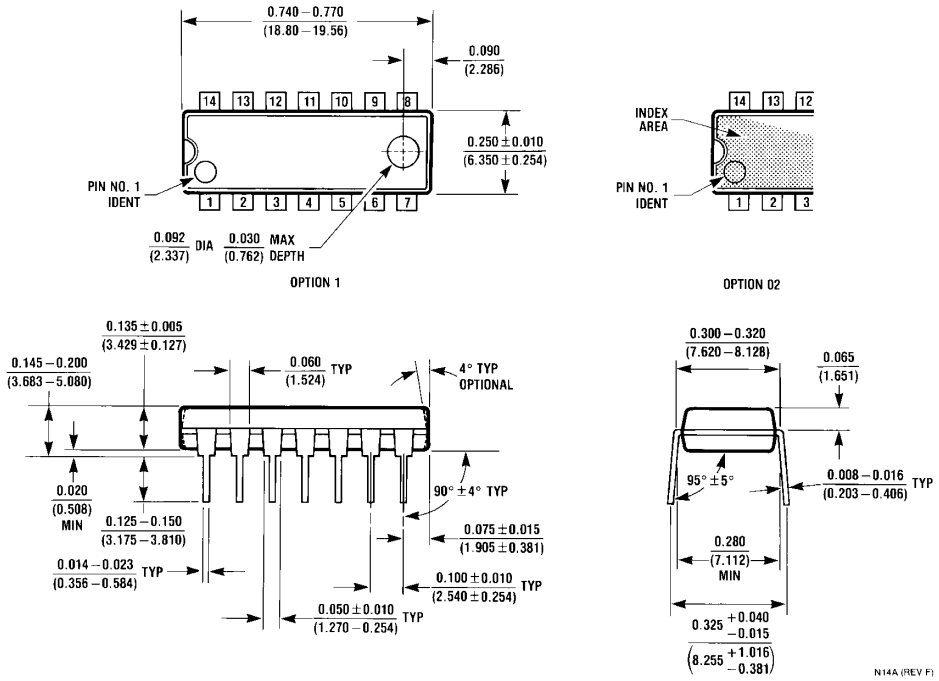


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F08
Quad 2-Input AND Gate

General Description

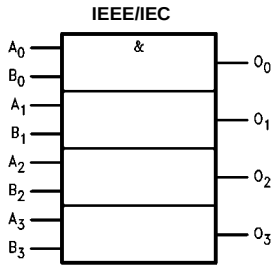
This device contains four independent gates, each of which performs the logic AND function.

Ordering Code:

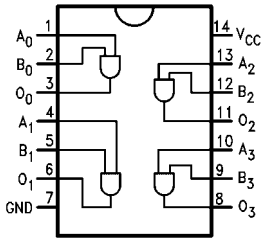
Order Number	Package Number	Package Description
74F08SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F08SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F08PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/1.0	20 μA/–0.6 mA
O_n	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

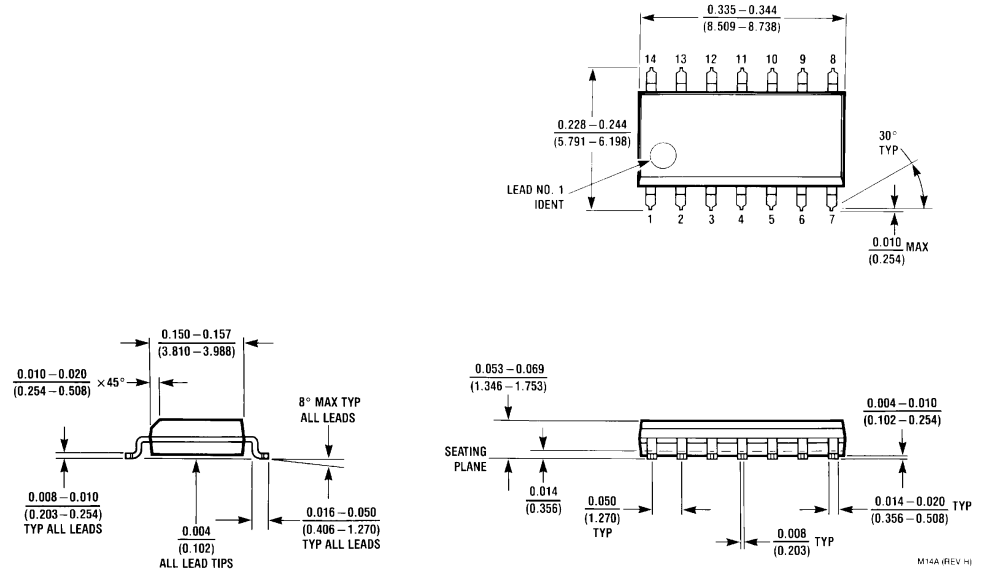
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			5.5	8.3	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			8.6	12.9	mA	Max	V_O = LOW

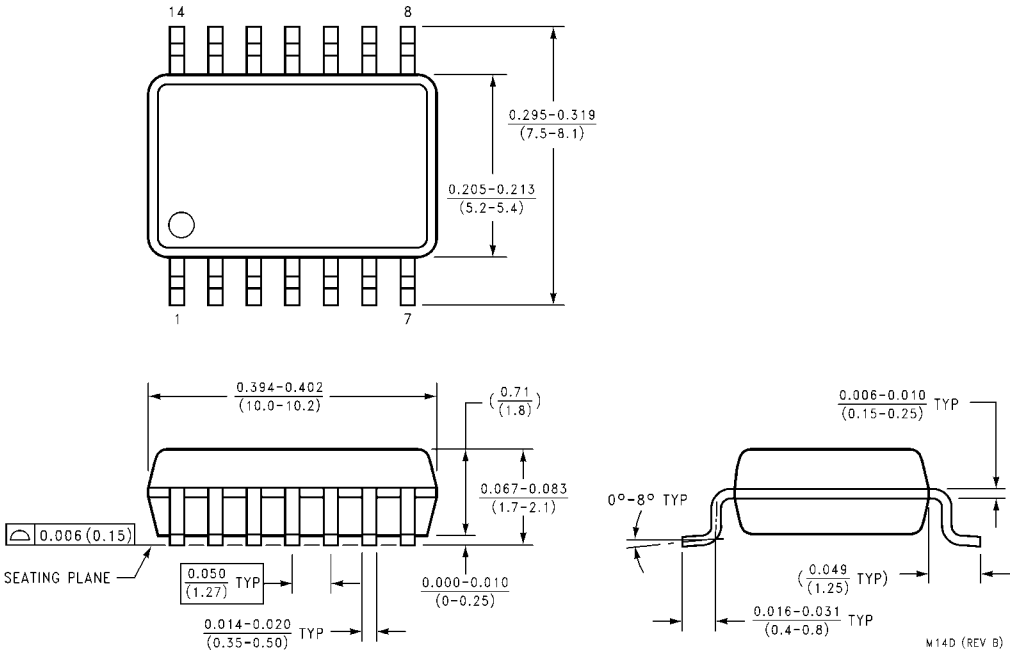
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	4.2	5.6	2.5	7.5	3.0	6.6	ns
t_{PHL}	A_n, B_n to O_n	2.5	4.0	5.3	2.0	7.5	2.5	6.3	

Physical Dimensions inches (millimeters) unless otherwise noted

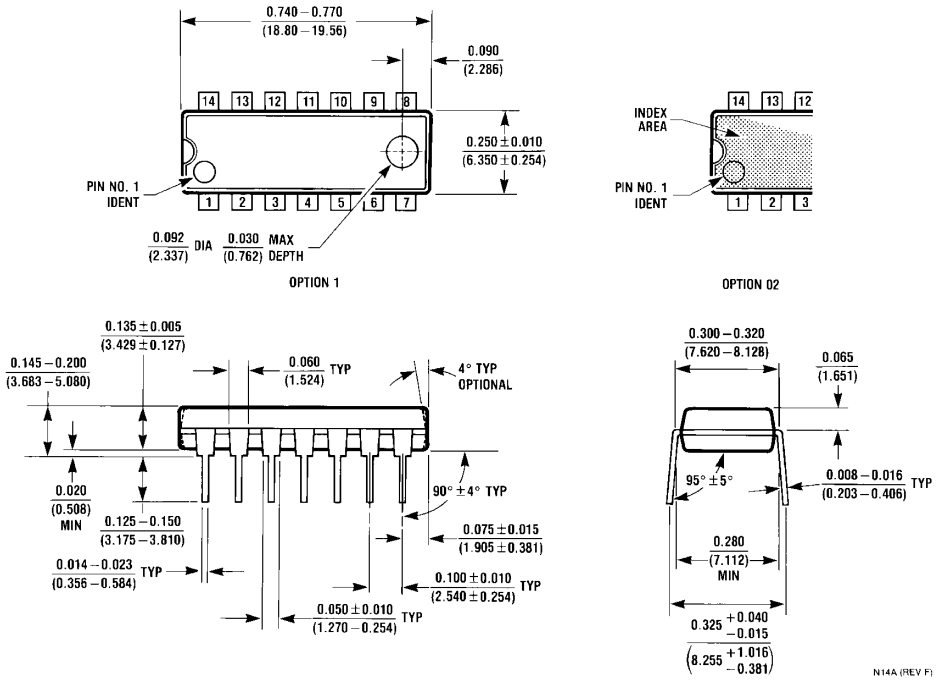


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F10
Triple 3-Input NAND Gate

General Description

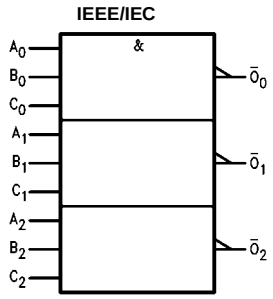
This device contains three independent gates, each of which performs the logic NAND function.

Ordering Code:

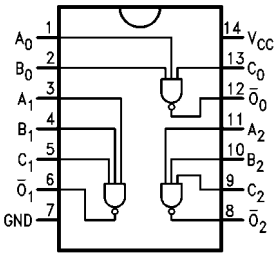
Order Number	Package Number	Package Description
74F10SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F10SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F10PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n, C_n	Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

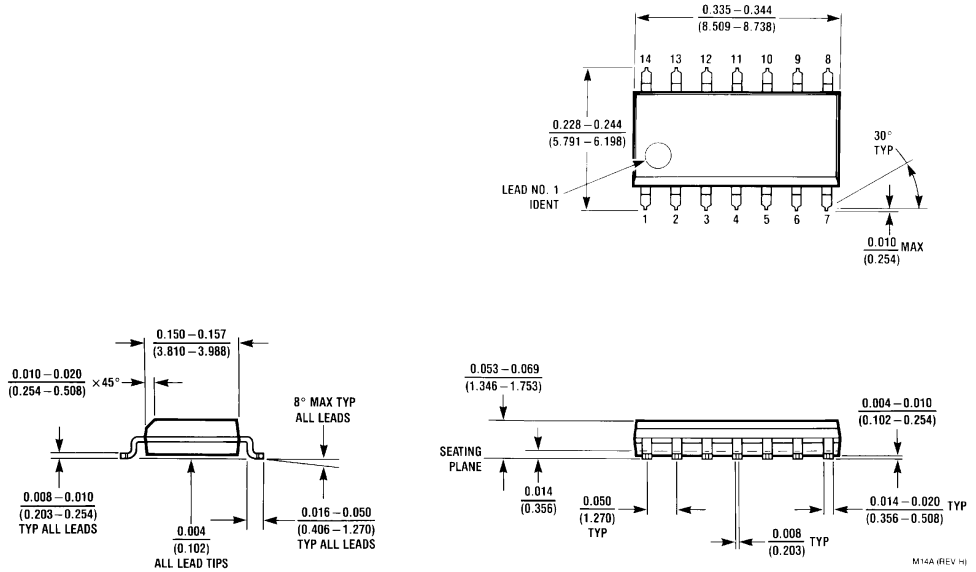
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			1.4	2.1	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			5.1	7.7	mA	Max	V_O = LOW

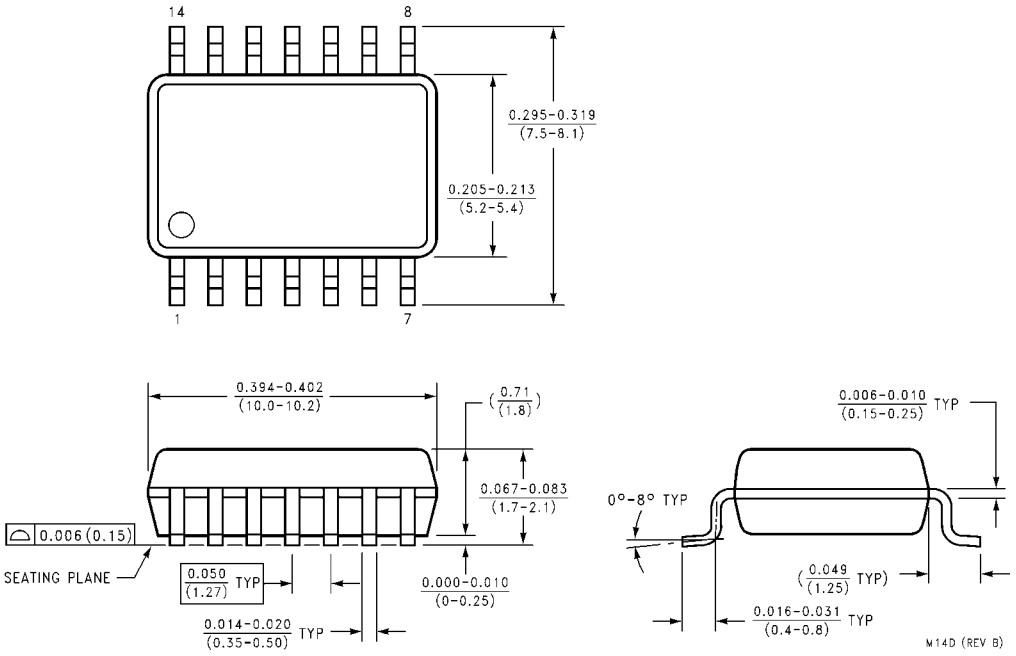
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	ns
t_{PHL}	A_n, B_n, C_n to $\overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3	

Physical Dimensions inches (millimeters) unless otherwise noted

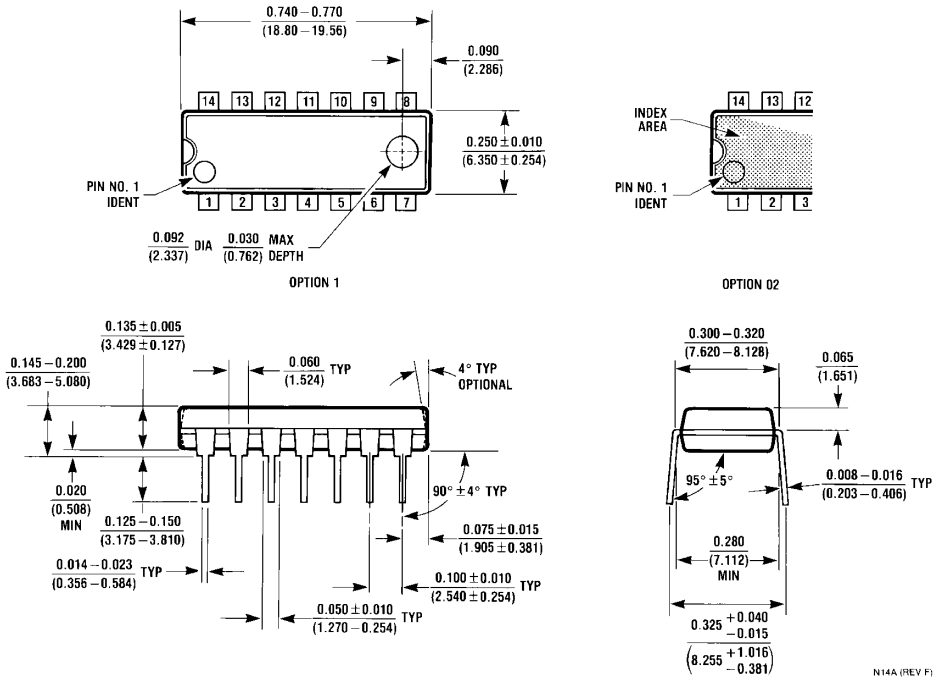


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

December 1993
Revised August 1999

74F1056
8-Bit Schottky Barrier Diode Array

General Description

The 74F1056 is an 8-bit Schottky barrier diode array designed to be employed as termination on the inputs to memory bus lines or CLOCK lines. This device is designed to suppress negative transients caused by line reflections, switching noise and crosstalk.

Features

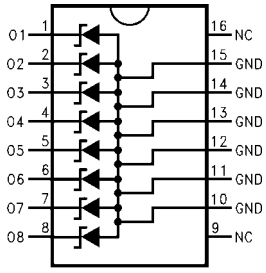
- 8-Bit array structure designed to suppress negative transients
- Guaranteed ESD protection (HBM) in excess of 4 kV
- Common anode shared by all eight diodes
- Broadside pinout for ease of bus routing

Ordering Code:

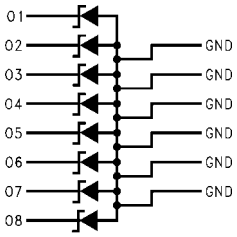
Order Number	Package Number	Package Description
74F1056SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Schematic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Operating Free-Air Temperature	0°C to 70°C
Steady State Reverse Voltage, (V_R)	7.0V
Continuous Total Power Dissipation at or below	
25°C Free-Air Temperature, (P_D)	750 mW
Continuous Forward Current, (I_f)	
Any Output Pin to GND	50 mA
Total Through All GND Pins	170 mA
Repetitive Peak Forward Current, Ifp (Note 2)	
Any Output Pin to GND	300 mA
Total Through All GND Pins	1.2A
ESD (HBM)	4 kV

Note 1: Absolute maximum ratings are valued beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: These values apply for the $t_w \leq 100$ µs, duty cycle ≤ 20%.

DC Electrical Characteristics

Over recommended operating free air temperature range, unless otherwise noted

SINGLE DIODE OPERATION (Note 3)

Symbol	Parameter	Min	Typ	Max	Units	Conditions
V_{BR}	Reverse Breakdown Voltage	7.0			V	I_R = 10 µA
I_R	Static Reverse Current			10	µA	V_R = 7V
V_F	Static Forward Voltage		−0.65	−0.85	V	I_F = −16 mA
			−0.8	−1.0		I_F = −50 mA
C_T	Total Capacitance		5	10	pF	V_I = 0V, f = 1 MHz
			4	8		V_I = 2V, f = 1 MHz

Note 3: These tests apply to separate diode operation, diodes not under test are open-circuit.

MULTIPLE DIODE OPERATION

Symbol	Parameter	Min	Typ	Max	Units	Conditions
I_{CR}	Internal Crosstalk Current		0.2	2	mA	Total GND current = 1.2A (Note 4)

Note 4: I_{CR} is measured under the following conditions: One diode static, all others switching

Switching diodes: t_W = 100 µs; Static diode: V_{IN} = 6V

Duty cycle = 20%, I_f = 200 mA

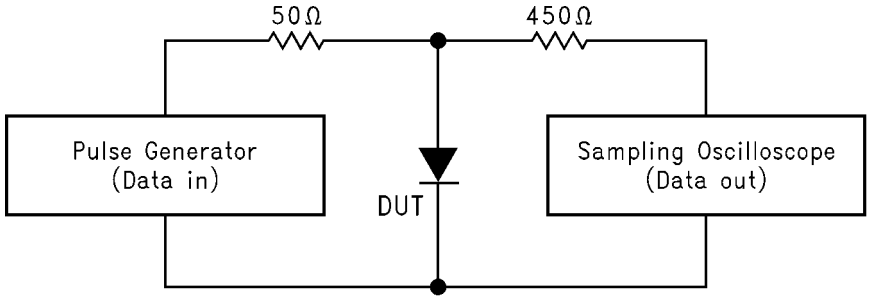
The static diode input current is the internal crosstalk current I_{CR}.

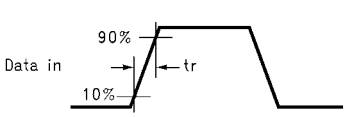
AC Electrical Characteristics

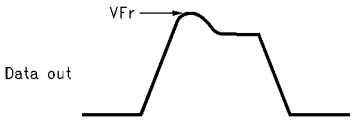
T_A = 25°C

Symbol	Parameter	Min	Typ	Max	Units	Conditions	Figure Number
V_{FR}	Forward Recovery Voltage		1.25		V	I_F = 300 mA	Figure 1
T_{RR}	Reverse Recovery Time			5.0	ns	I_F = 10 mA, I_R = 1 mA	Figure 2
						R_L = 100Ω	

AC Loading and Waveforms

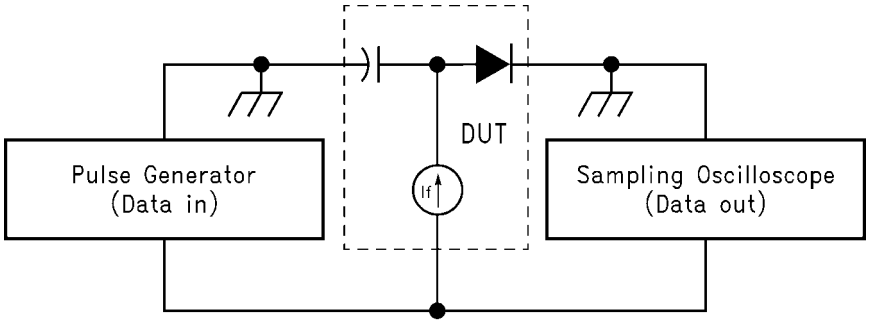


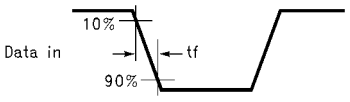


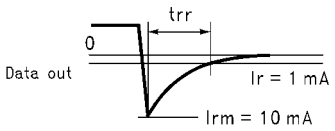


t_r = 20 ns, Z_O = 50Ω, freq = 500 Hz

FIGURE 1. Forward Recovery Voltage







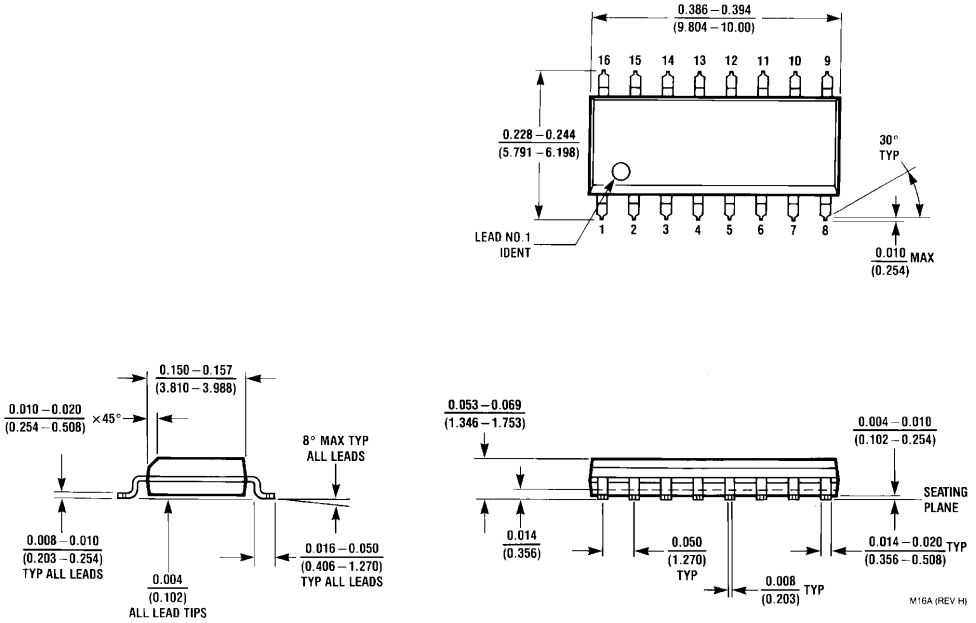
t_f = 0.5 ns, Z_O = 50Ω, t_W = 50 ns, duty cycle = 0.01

R_L = 100Ω (Note)

Monitored by Oscilloscope having the following characteristics: $t_r \leq 350$ ps, R_I = 50Ω, C_I = 5 pF.

FIGURE 2. Reverse Recovery Time

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A

FAIRCHILD SEMICONDUCTOR™

October 1994
Revised August 1999

74F1071
18-Bit Undershoot/Overshoot Clamp and ESD Protection Device

General Description

The 74F1071 is an 18-bit undershoot/overshoot clamp which is designed to limit bus voltages and also to protect more sensitive devices from electrical overstress due to electrostatic discharge (ESD). The inputs of the device aggressively clamp voltage excursions nominally at 0.5V below and 7V above ground.

Features

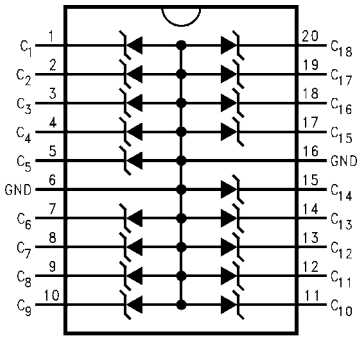
- 18-bit array structure in 20-pin package
- FAST® Bipolar voltage clamping action
- Dual center pin grounds for min inductance
- Robust design for ESD protection
- Low input capacitance
- Optimum voltage clamping for 5V CMOS/TTL applications

Ordering Code:

Order Number	Package Number	Package Description
74F1071SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F1071MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F1071MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Note: Simplified Component Representation

FAST® is a registered trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−65°C to +125°C
Junction Temperature under Bias	−65°C to +150°C
Input Voltage (Note 2)	−0.5V to +6V
Input Current (Note 2)	−200 mA to +50 mA
ESD (Note 3)	
Human Body Model	
(MIL-STD-883D method 3015.7)	±10 kV
IEC 801-2	±6 kV
Machine Model (EIAJIC-121-1981)	±2 kV
DC Latchup Source Current	
(JEDEC Method 17)	±500 mA
Package Power Dissipation @+70°C	
SOIC Package	800 mW

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Reverse Bias Voltage	0V to 5.25 V_{DC}
Thermal Resistance (θ_{JA} in Free Air)	
SOIC Package	100°C/W
SSOP Package	110°C/W

Note 1: Absolute maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Voltage ratings may be exceeded if current ratings and junction temperature and power consumption ratings are not exceeded.

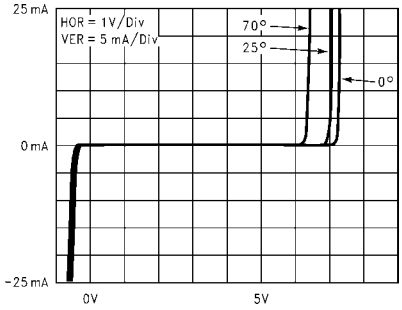
Note 3: ESD Rating for Direct contact discharge using ESD Simulation Tester. Higher rating may be realized in the actual application.

DC Electrical Characteristics

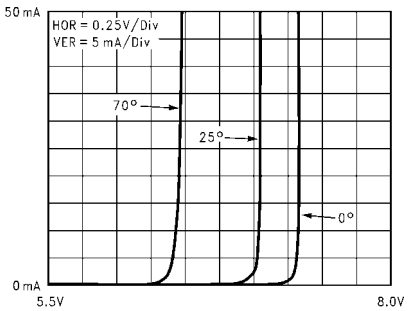
Symbol	Parameter	T_A = +25°C			T_A = 0°C to +70°C		Units	Conditions
		Min	Typ	Max	Min	Max		
I_{IH}	Input HIGH Current		1.5	10		50	µA	V_{IN} = 5.25V; Untested Input @ GND
			3	20		100		V_{IN} = 5.5V; Untested Input @ GND
V_Z	Reverse Voltage	6.6	6.9	7.2	5.9	7.7	V	I_Z = 1 mA; Untested Inputs @ GND
			7.1	7.5		8.0		I_Z = 50 mA; Untested Inputs @ GND
V_F	Forward Voltage	−0.3	−0.6	−0.9	−0.3	−0.9	V	I_F = −18 mA; Untested Inputs @ 5V
		−0.5	−1.1	−1.5	−0.5	−1.5		I_F = −200 mA; Untested Inputs @ 5V
I_{CT}	Adjacent Input Crosstalk			3			%	
C_{IN}	Input Capacitance		25				pF	V_{BIAS} = 0 V_{DC}
	(small signal @ 1 MHz)		13					V_{BIAS} = 5 V_{DC}

DC Electrical Characteristics

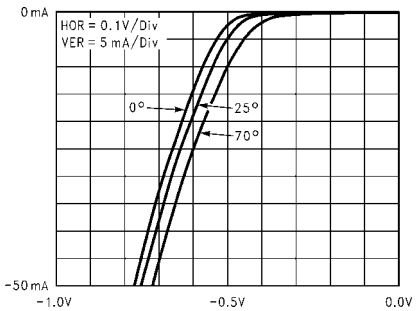
Typical Forward and Reverse V/I Characteristics

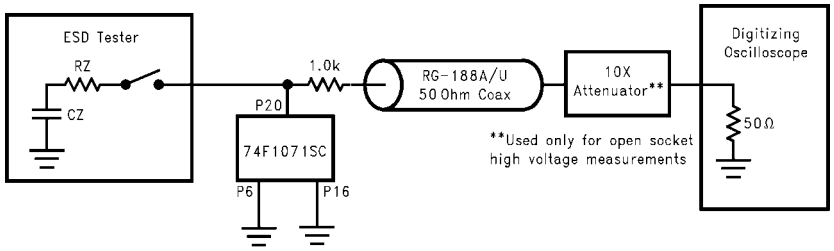


Typical Reverse Conduction Characteristics



Typical Forward Conduction Characteristics



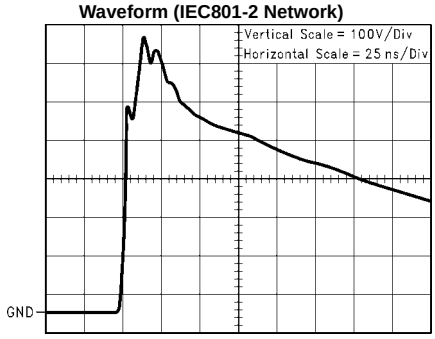


ESD Network	CZ	RZ
Human Body Model	100 pF	1500Ω
IEC 801-2	150 pF	330Ω

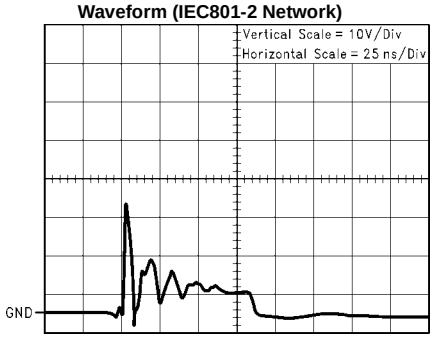
Simulated ESD Voltage Clamping Test Circuit

DC Electrical Characteristics (Continued)

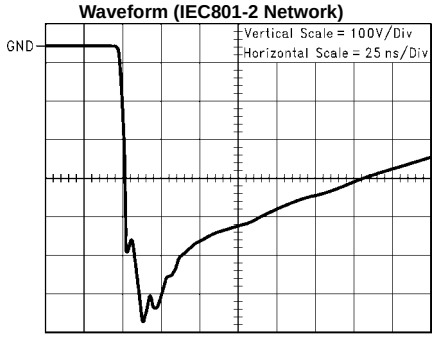
Unclamped + 1 KV ESD Voltage Waveform (IEC801-2 Network)



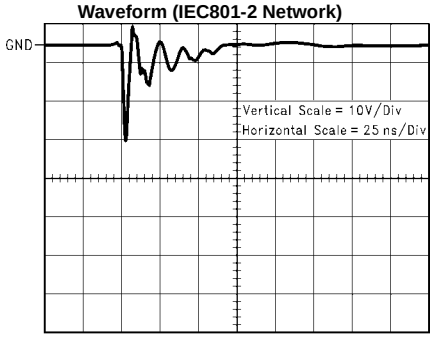
Clamped + 1 KV ESD Voltage Waveform (IEC801-2 Network)



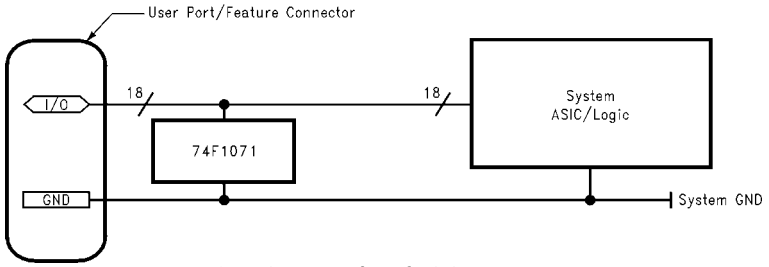
Unclamped - 1 KV ESD Voltage Waveform (IEC801-2 Network)



Clamped - 1 KV ESD Voltage Waveform (IEC801-2 Network)

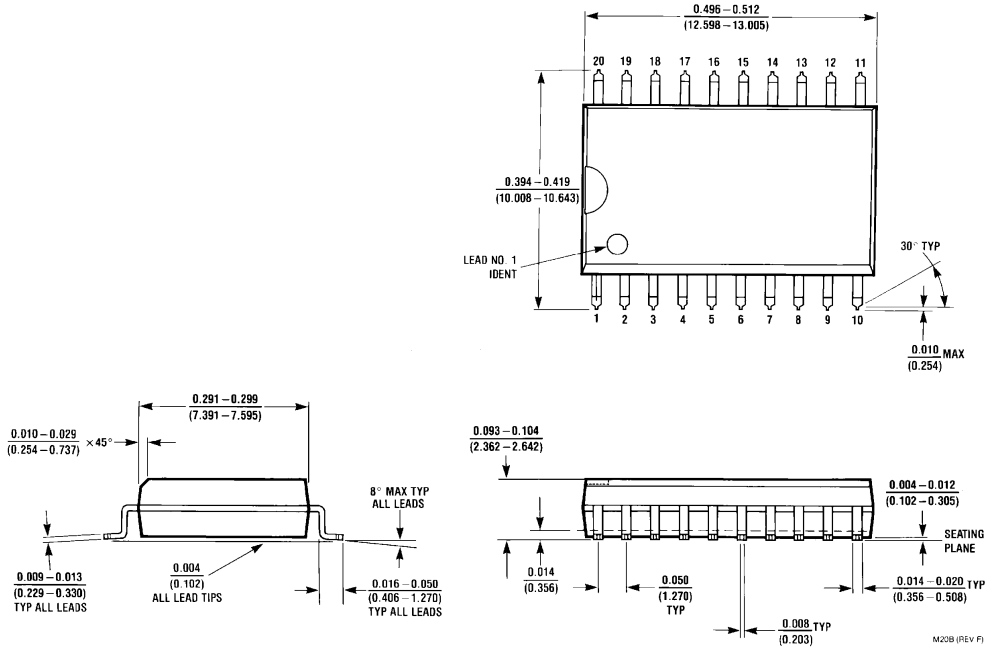


Typical Application

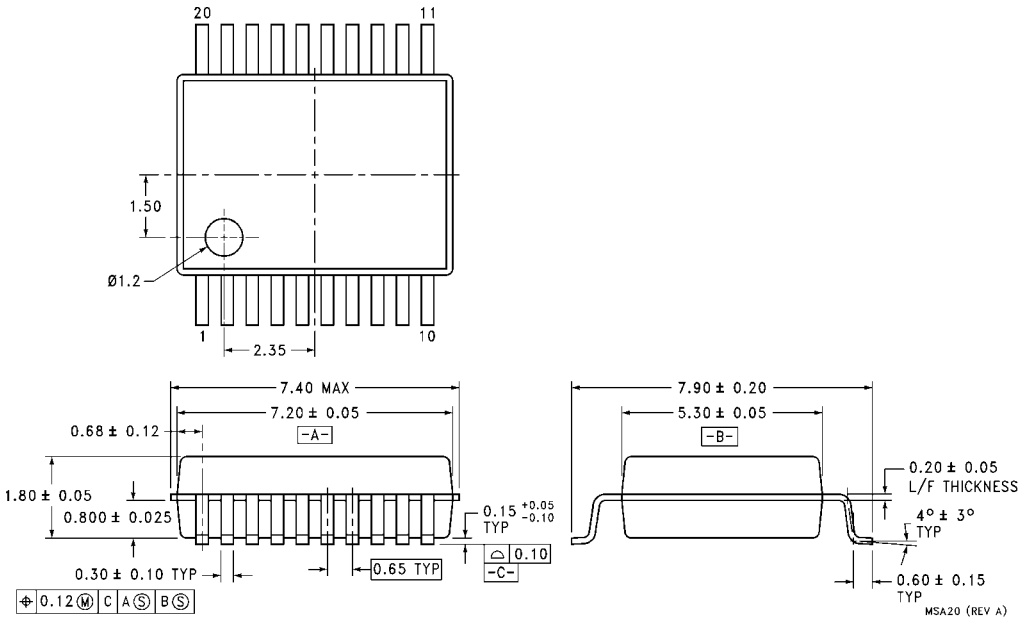


74F1071 ESD Protection of ASIC on User Port

Physical Dimensions inches (millimeters) unless otherwise noted

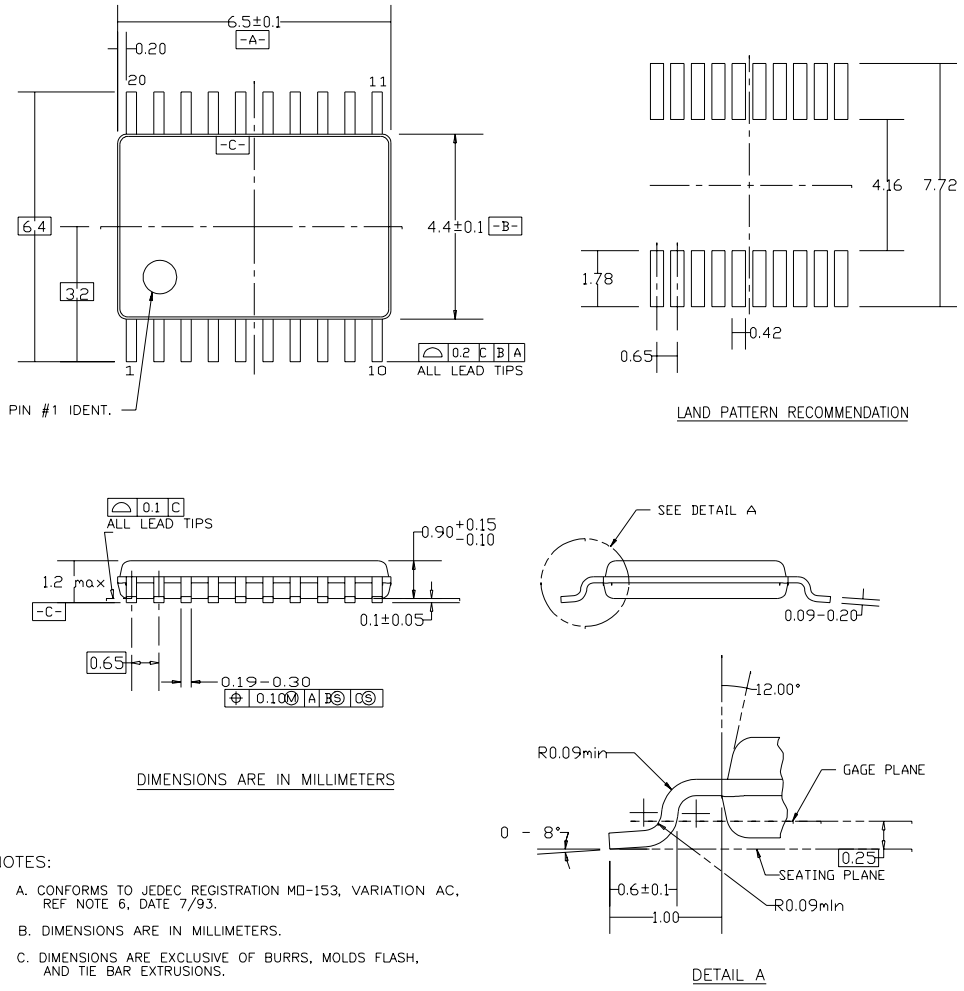


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised November 1999

74F109
Dual JK Positive Edge-Triggered Flip-Flop

General Description

The F109 consists of two high-speed, completely independent transition clocked $\overline{JK}$ flip-flops. The clocking operation is independent of rise and fall times of the clock waveform. The $\overline{JK}$ design allows operation as a D-type flip-flop (refer to F74 data sheet) by connecting the J and $\overline{K}$ inputs.

Asynchronous Inputs:

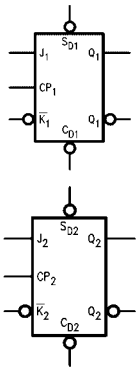
- LOW input to $\overline{S}_D$ sets Q to HIGH level
- LOW input to $\overline{C}_D$ sets Q to LOW level
- Clear and Set are independent of clock
- Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Ordering Code:

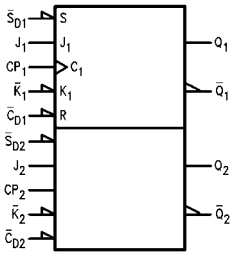
Order Number	Package Number	Package Description
74F109SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
74F109SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE 11, 5.3mm Wide
74F109PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Devices also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

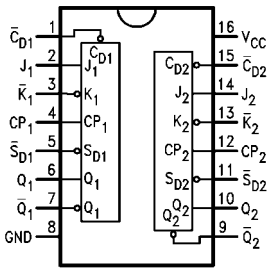
Logic Symbols



IEEE/IEC



Connection Diagram



Truth Table

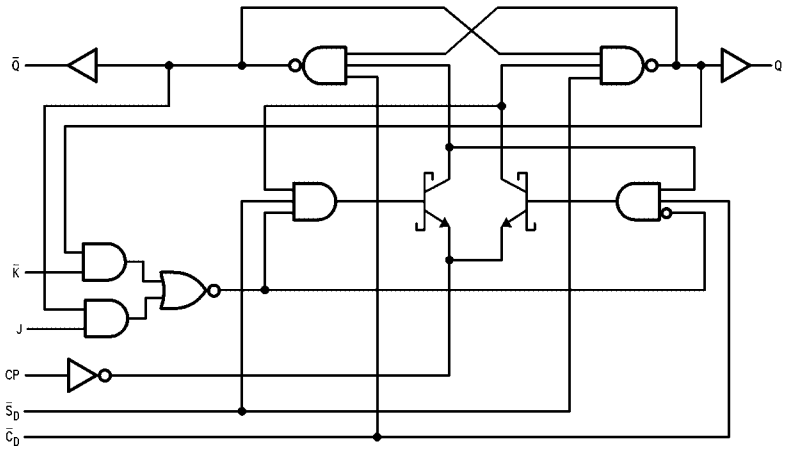
Inputs					Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	J	$\overline{K}$	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	l	l	L	H
H	H	⌐	h	l	Toggle	
H	H	⌐	l	h	Q	$\overline{Q}$
H	H	⌐	h	h	H	L
H	H	L	X	X	Q	$\overline{Q}$

H (h) = HIGH Voltage Level
L (l) = LOW Voltage Level
⌐ = LOW-to-HIGH Transition
X = Immaterial
Q_0 ($\overline{Q}_0$) = Before LOW-to-HIGH Transition of Clock
Lower case letters indicate the state of the referenced output one setup time prior to the LOW-to-HIGH clock transition.

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
J_1, J_2, $\overline{K}_1$, $\overline{K}_2$	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP_1, CP_2	Clock Pulse Inputs (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs (Active LOW)	1.0/3.0	20 μA/–1.8 mA
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs (Active LOW)	1.0/3.0	20 μA/–1.8 mA
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs	50/33.3	–1 mA/20 mA

Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{cc} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (J_n, $\overline{K}_n$)
					−1.8	mA	Max	V_{IN} = 0.5V ($\overline{C}_{Dn}$, $\overline{S}_{Dn}$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			11.7	17.0	mA	Max	CP = 0V

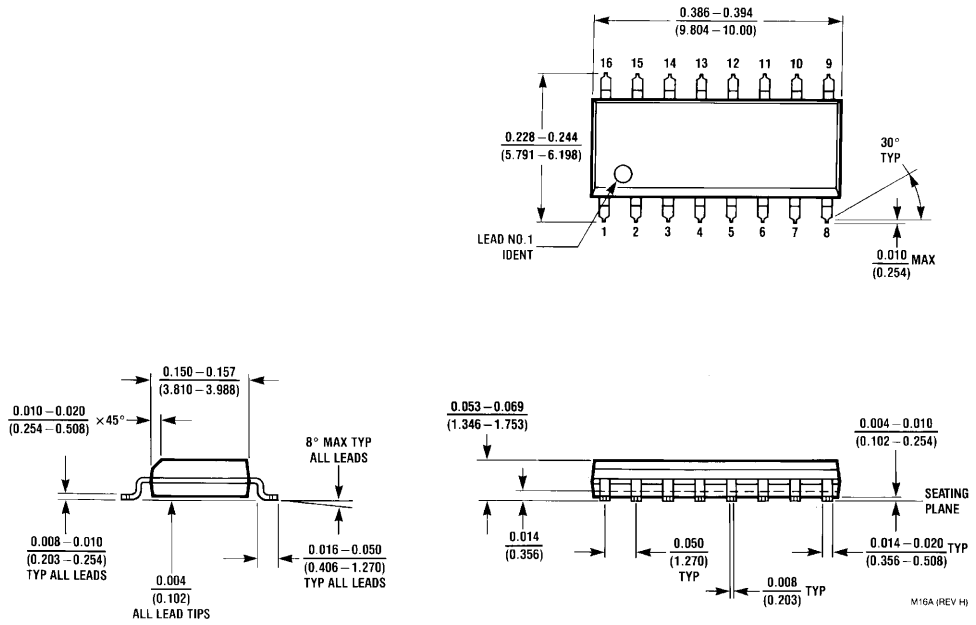
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	125		90		MHz
t_{PLH}	Propagation Delay	3.8	5.3	7.0	3.8	8.0	ns
t_{PHL}	CP_n to Q_n or $\overline{Q}_n$	4.4	6.2	8.0	4.4	9.2	
t_{PLH}	Propagation Delay	3.2	5.2	7.0	3.2	8.0	ns
t_{PHL}	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.5	7.0	9.0	3.5	10.5	ns

AC Operating Requirements

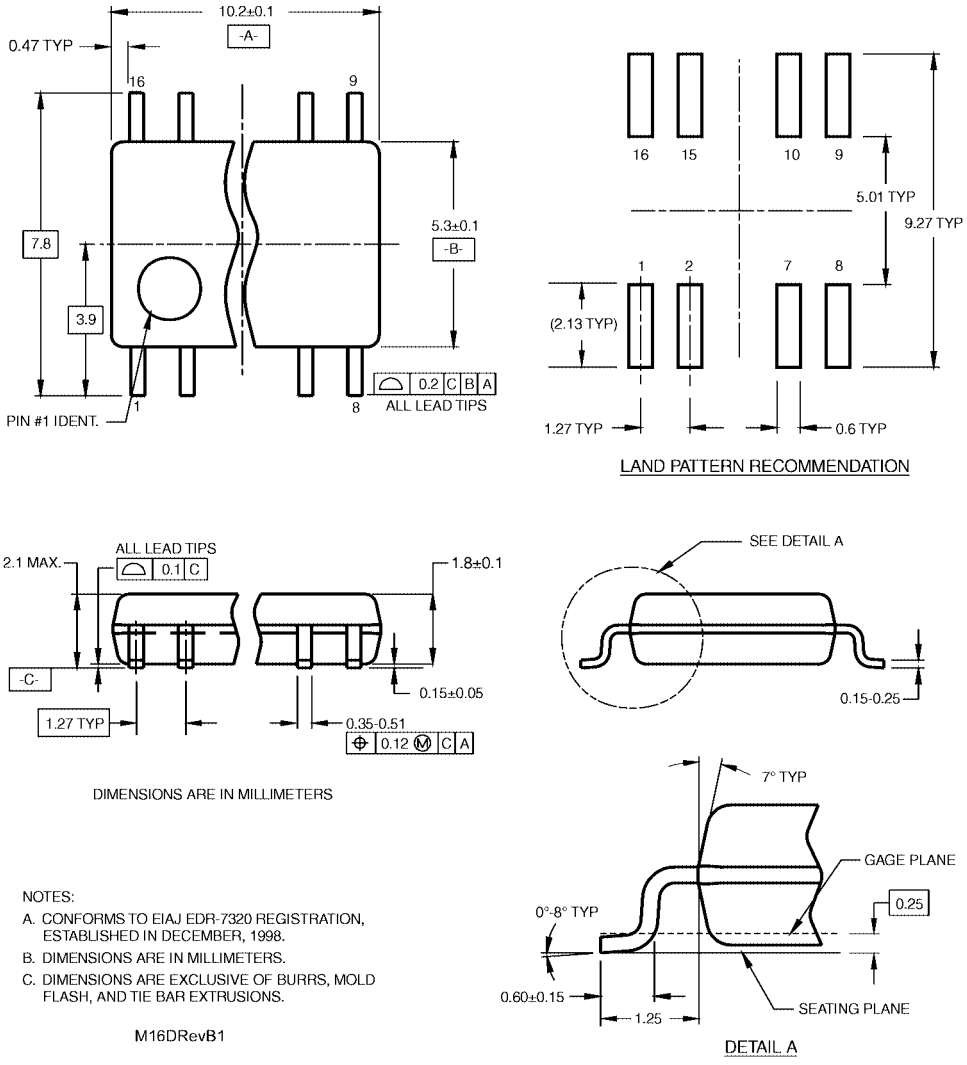
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.0		ns
$t_S(L)$	J_n or $\overline{K}_n$ to CP_n	3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.0		
$t_H(L)$	J_n or $\overline{K}_n$ to CP_n	1.0		1.0		
$t_W(H)$	CP_n Pulse Width	4.0		4.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		
$t_W(L)$	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ Pulse Width LOW	4.0		4.0		ns
t_{REC}	Recovery Time $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP	2.0		2.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

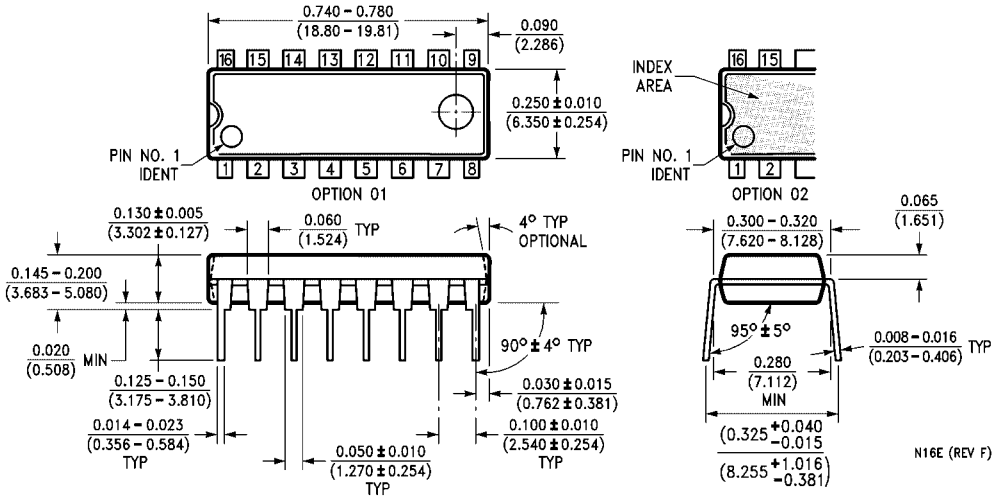
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M16DRevB1

16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F11
Triple 3-Input AND Gate

General Description

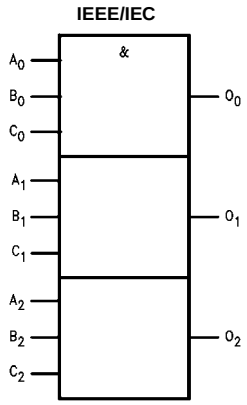
This device contains three independent gates, each of which performs the logic AND function.

Ordering Code:

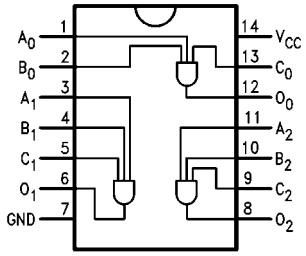
Order Number	Package Number	Package Description
74F11SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F11SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F11PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n, C_n	Inputs	1.0/1.0	20 µA/–0.6 mA
O_n	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

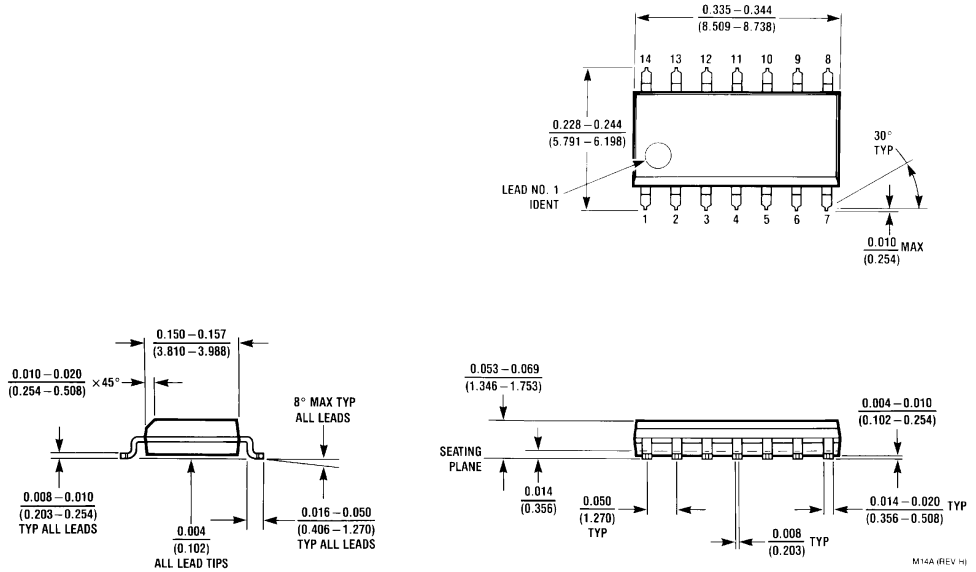
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			4.1	6.2	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			6.5	9.7	mA	Max	V_O = LOW

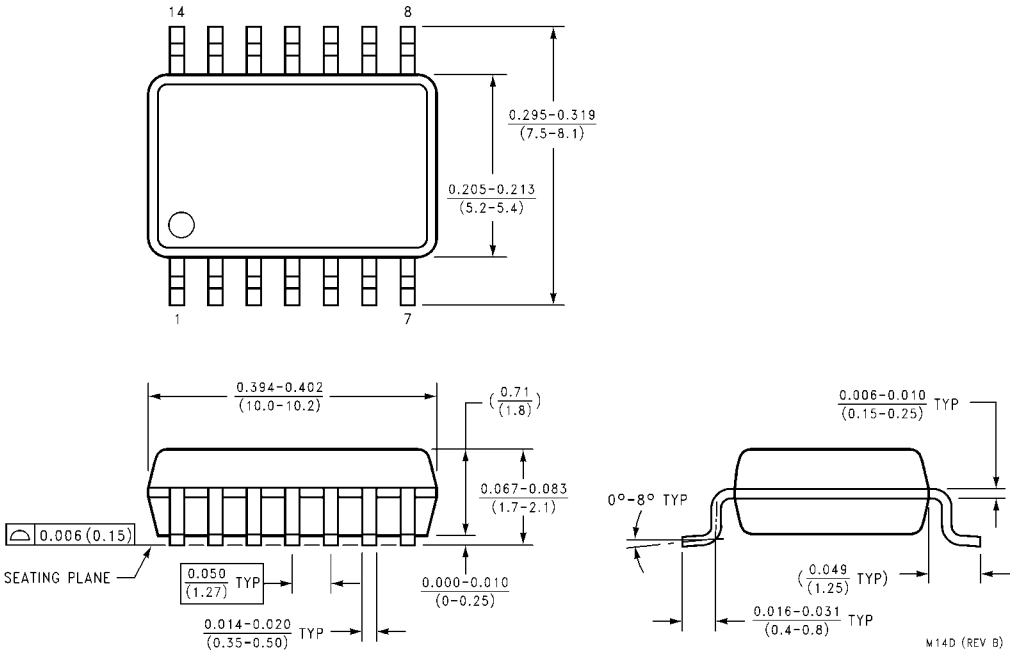
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	4.2	5.6	2.5	7.5	3.0	6.6	ns
t_{PHL}	A_n, B_n, C_n to O_n	2.5	4.1	5.5	2.0	7.5	2.5	6.5	

Physical Dimensions inches (millimeters) unless otherwise noted

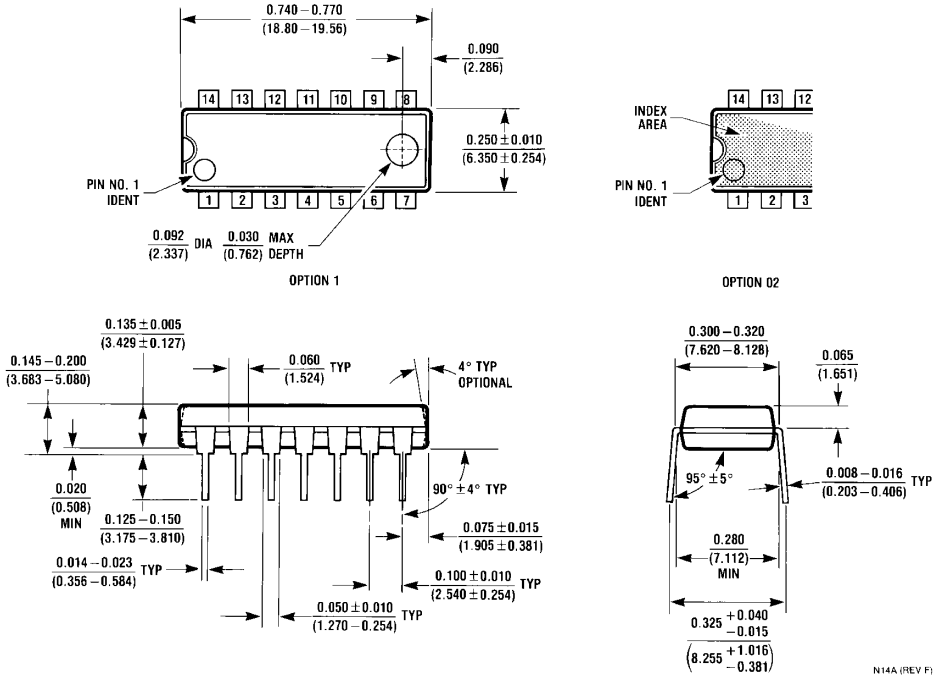


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F112
Dual JK Negative Edge-Triggered Flip-Flop

General Description

The 74F112 contains two independent, high-speed JK flip-flops with Direct Set and Clear inputs. Synchronous state changes are initiated by the falling edge of the clock. Triggering occurs at a voltage level of the clock and is not directly related to the transition time. The J and K inputs can change when the clock is in either state without affecting the flip-flop, provided that they are in the desired state during the recommended setup and hold times relative to the falling edge of the clock. A LOW signal on $\overline{S}_D$ or $\overline{C}_D$ prevents clocking and forces Q or $\overline{Q}$ HIGH, respectively.

Simultaneous LOW signals on $\overline{S}_D$ and $\overline{C}_D$ force both Q and $\overline{Q}$ HIGH.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ sets Q to HIGH level

LOW input to $\overline{C}_D$ sets Q to LOW level

Clear and Set are independent of clock

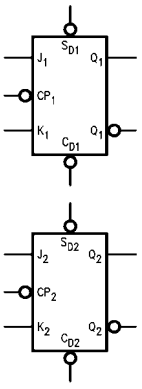
Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Ordering Code:

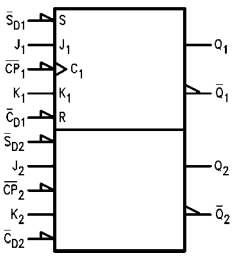
Order Number	Package Number	Package Description
74F112SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F112SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F112PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

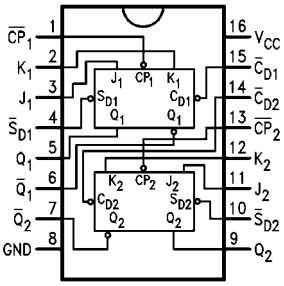
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
J_1, J_2, K_1, K_2	Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{CP}_1$, $\overline{CP}_2$	Clock Pulse Inputs (Active Falling Edge)	1.0/4.0	20 µA/–2.4 mA
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs (Active LOW)	1.0/5.0	20 µA/–3.0 mA
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs (Active LOW)	1.0/5.0	20 µA/–3.0 mA
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs	50/33.3	–1 mA/20 mA

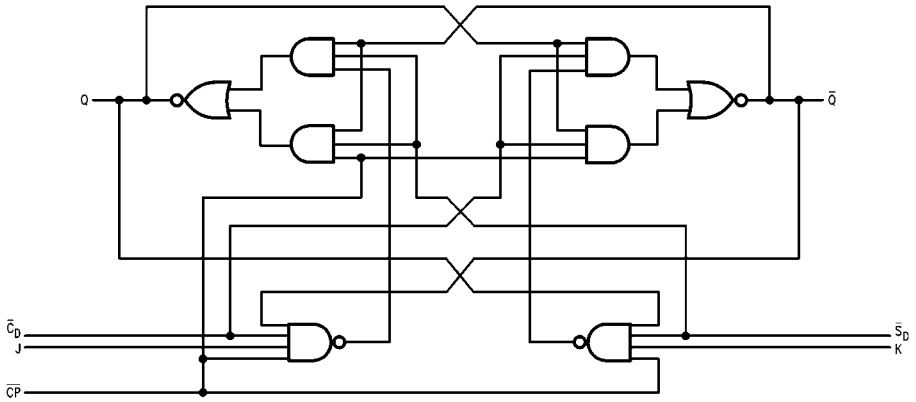
Truth Table

Inputs					Outputs	
$\overline{S}_D$	$\overline{C}_D$	$\overline{CP}$	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	h	h	$\overline{Q}_0$	Q_0
H	H	⌐	l	h	L	H
H	H	⌐	h	l	H	L
H	H	⌐	l	l	Q_0	$\overline{Q}_0$

H (h) = HIGH Voltage Level
L (l) = LOW Voltage Level
X = Immaterial
⌐ = HIGH-to-LOW Clock Transition
$Q_0(\overline{Q}_0)$ = Before HIGH-to-LOW Transition of Clock
Lower case letters indicate the state of the referenced input or output one setup time prior to the HIGH-to-LOW clock transition.

Logic Diagram

(One Half Shown)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (J_n, K_n)
					−2.4			V_{IN} = 0.5V ($\overline{CP}_n$)
					−3.0			V_{IN} = 0.5V ($\overline{C}_{Dn}$, $\overline{S}_{Dn}$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			12	19	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			12	19	mA	Max	V_O = LOW

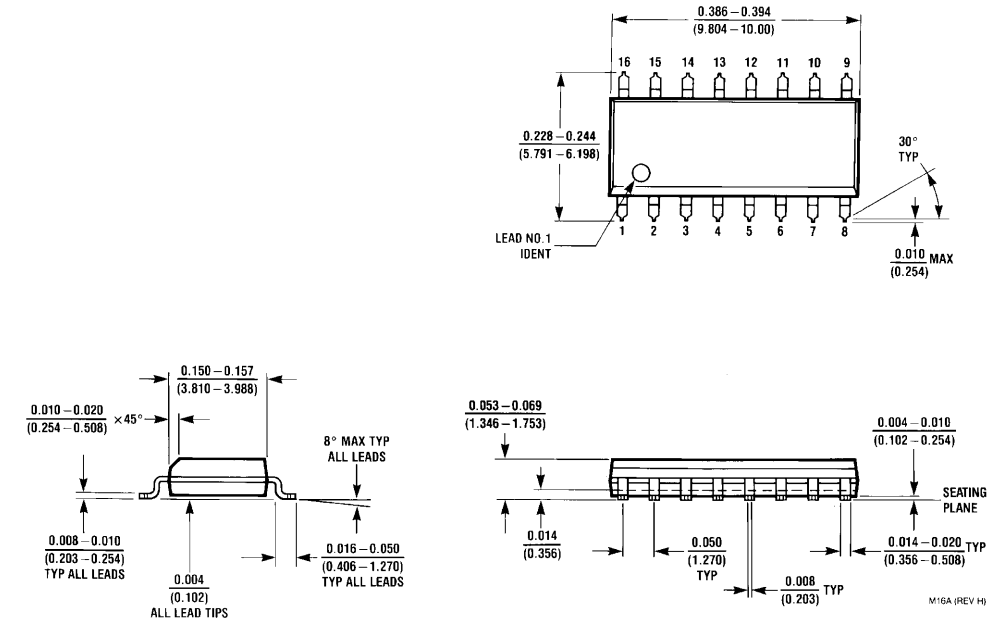
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	85	105		80		MHz
t_{PLH}	Propagation Delay	2.0	5.0	6.5	2.0	7.5	ns
t_{PHL}	$\overline{CP}_n$ to Q_n or $\overline{Q}_n$	2.0	5.0	6.5	2.0	7.5	
t_{PLH}	Propagation Delay	2.0	4.5	6.5	2.0	7.5	ns
t_{PHL}	$\overline{C}_{Dn}$, $\overline{S}_{Dn}$ to $\overline{Q}_n$, $\overline{Q}_n$	2.0	4.5	6.5	2.0	7.5	

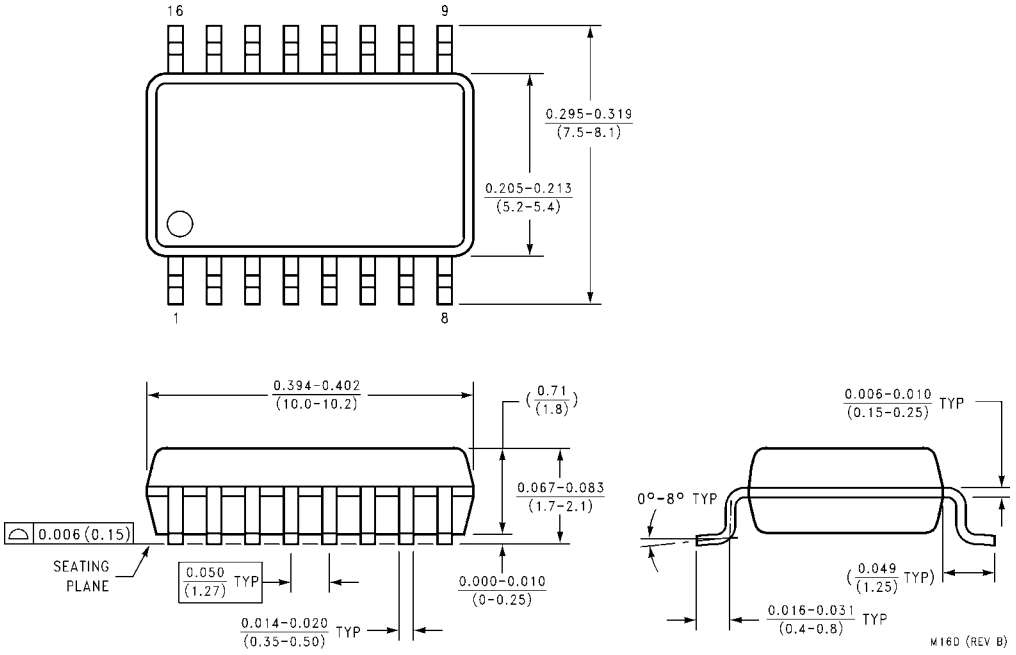
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		5.0		ns
$t_S(L)$	J_n or K_n to $\overline{CP}_n$	3.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	J_n or K_n to $\overline{CP}_n$	0		0		
$t_W(H)$	$\overline{CP}$ Pulse Width	4.5		5.0		ns
$t_W(L)$	HIGH or LOW	4.5		5.0		
$t_W(L)$	Pulse Width, LOW $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$	4.5		5.0		ns
t_{REC}	Recovery Time $\overline{S}_{Dn}$, $\overline{C}_{Dn}$ to $\overline{CP}$	4.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

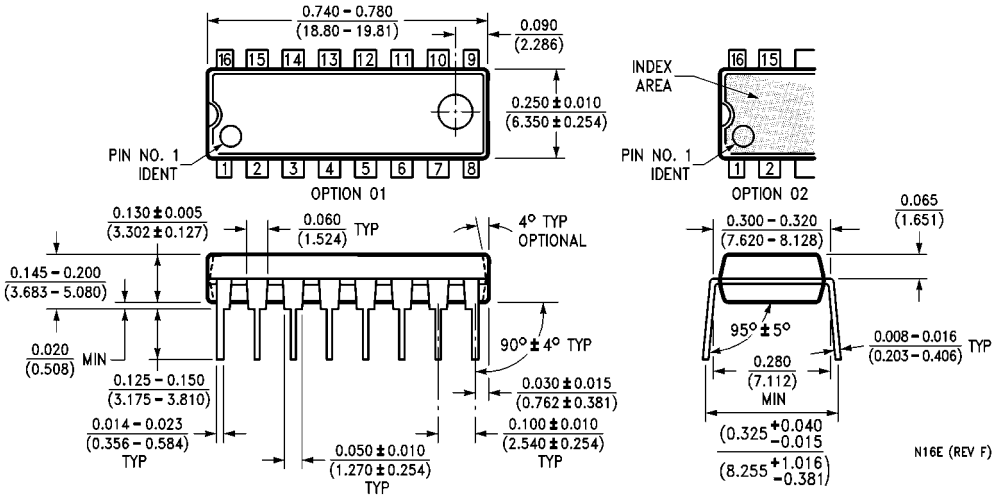


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F113
Dual JK Negative Edge-Triggered Flip-Flop

General Description

The 74F113 offers individual J, K, Set and Clock inputs. When the clock goes HIGH the inputs are enabled and data may be entered. The logic level of the J and K inputs may be changed when the clock pulse is HIGH and the flip-flop will perform according to the Truth Table as long as minimum setup and hold times are observed. Input data is transferred to the outputs on the falling edge of the clock pulse.

Asynchronous input:

LOW input to $\overline{S}_D$ sets Q to HIGH level

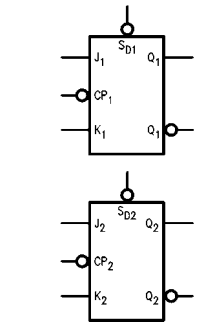
Set is independent of clock

Ordering Code:

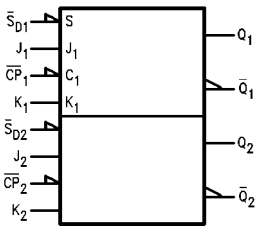
Order Number	Package Number	Package Description
74F113SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F113SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F113PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

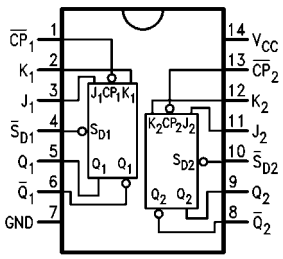
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
J_1, J_2, K_1, K_2	Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{CP}_1$, $\overline{CP}_2$	Clock Pulse Inputs (Active Falling Edge)	1.0/4.0	20 μA/–2.4 mA
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs (Active LOW)	1.0/5.0	20 μA/–3.0 mA
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs	50/33.3	–1 mA/20 mA

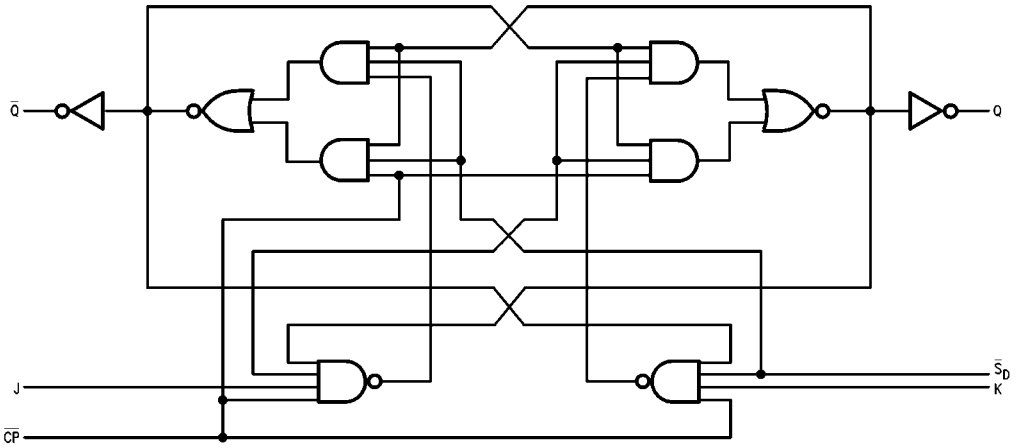
Truth Table

Inputs				Outputs	
$\overline{S}_D$	$\overline{CP}$	J	K	Q	$\overline{Q}$
L	X	X	X	H	L
H	⌐	h	h	$\overline{Q}_0$	Q_0
H	⌐	l	h	L	H
H	⌐	h	l	H	L
H	⌐	l	l	Q_0	$\overline{Q}_0$

H (h) = HIGH Voltage Level
L (l) = LOW Voltage level
⌐ = HIGH-to-LOW Clock Transition
X = Immaterial
Q_0 ($\overline{Q}_0$) = Before HIGH-to-LOW Transition of Clock
Lower case letters indicate the state of the referenced input or output prior to the HIGH-to-LOW clock transition.

Logic Diagram

(One Half Shown)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (J_n, K_n)
					−2.4			V_{IN} = 0.5V ($\overline{CP}_n$)
					−3.0			V_{IN} = 0.5V ($\overline{S}_{Dn}$)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			12	19	mA	Max	

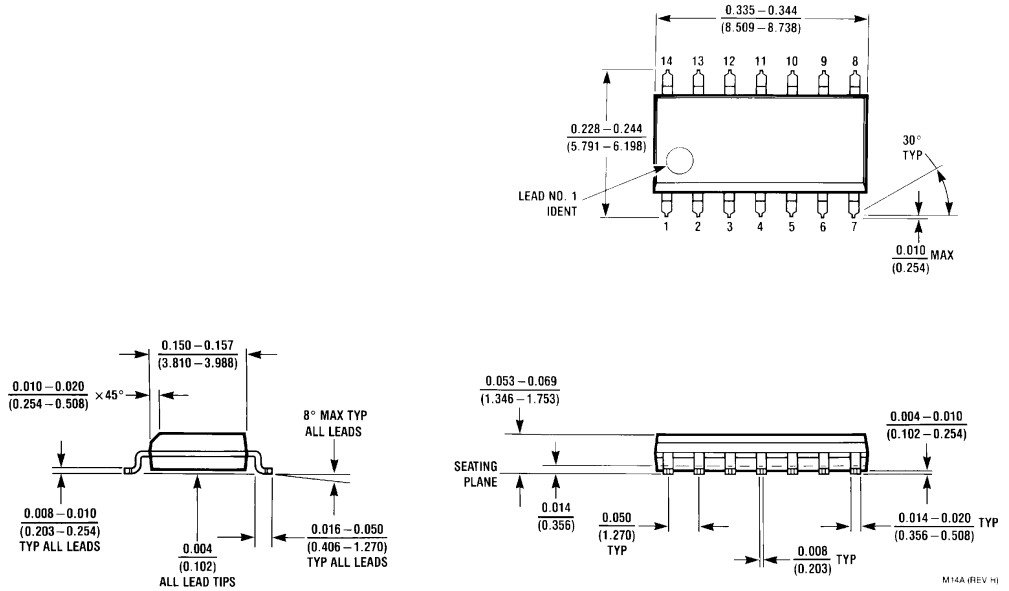
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	85	105		80		MHz
t_{PLH}	Propagation Delay	2.0	4.0	6.0	2.0	7.0	ns
t_{PHL}	$\overline{CP}_n$ to Q_n or $\overline{Q}_n$	2.0	4.0	6.0	2.0	7.0	
t_{PLH}	Propagation Delay	2.0	4.5	6.5	2.0	7.5	ns
t_{PHL}	$\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	2.0	4.5	6.5	2.0	7.5	

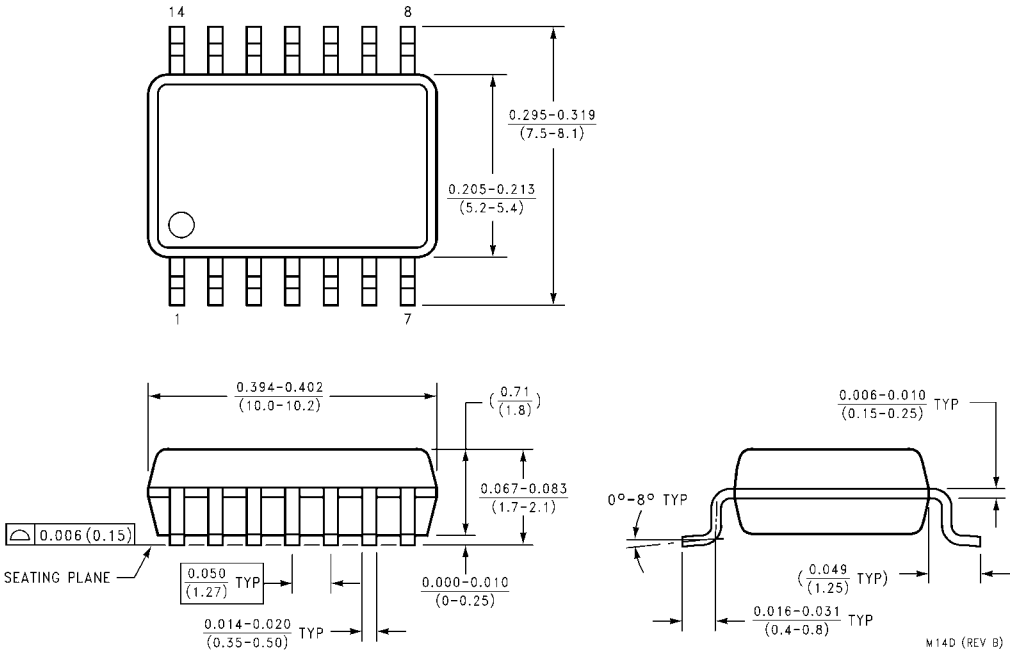
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		5.0		ns
$t_S(L)$	J_n or K_n to $\overline{CP}_n$	3.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	J_n or K_n to $\overline{CP}_n$	0		0		
$t_W(H)$	$\overline{CP}_n$ Pulse Width	4.5		5.0		ns
$t_W(L)$	HIGH or LOW	4.5		5.0		
$t_W(L)$	$\overline{S}_{Dn}$ Pulse Width, LOW	4.5		5.0		ns
t_{REC}	$\overline{S}_{Dn}$ to $\overline{CP}_n$ Recovery Time	4.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

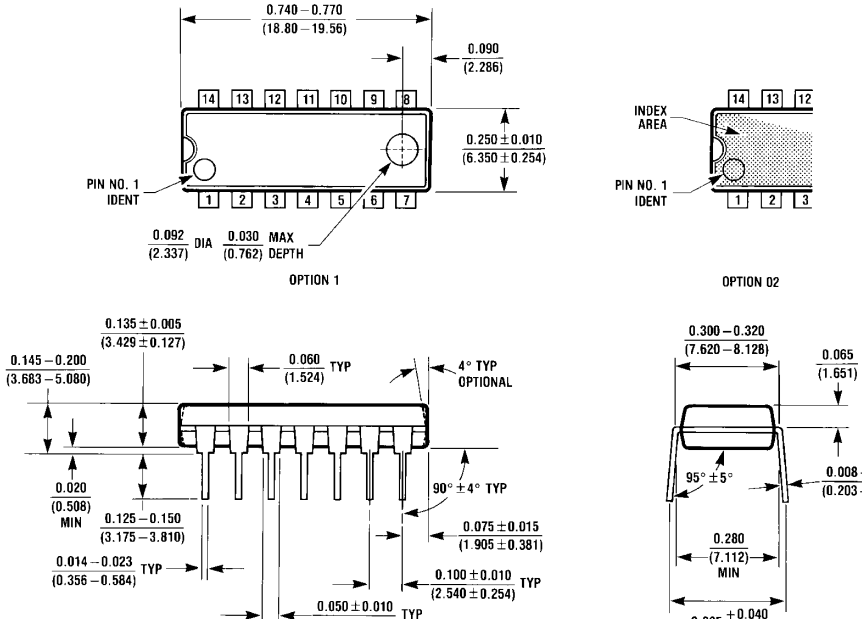


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F114
Dual JK Negative Edge-Triggered Flip-Flop with Common Clocks and Clears

General Description

The 74F114 contains two high-speed JK flip-flops with common Clock and Clear inputs. Synchronous state changes are initiated by the falling edge of the clock. Triggering occurs at a voltage level of the clock and is not directly related to the transition time. The J and K inputs can change when the clock is in either state without affecting the flip-flop, provided that they are in the desired state during the recommended setup and hold times relative to the falling edge of the clock. A LOW signal on $\overline{S}_D$ or $\overline{C}_D$ prevents clocking and forces Q or $\overline{Q}$ HIGH, respectively.

Simultaneous LOW signals on $\overline{S}_D$ and $\overline{C}_D$ force both Q and $\overline{Q}$ HIGH.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ sets Q to HIGH level

LOW input to $\overline{C}_D$ sets Q to LOW level

Clear and Set are independent of Clock

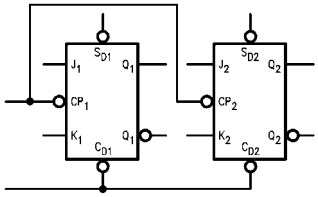
Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Ordering Code:

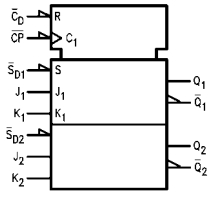
Order Number	Package Number	Package Description
74F114SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F114PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

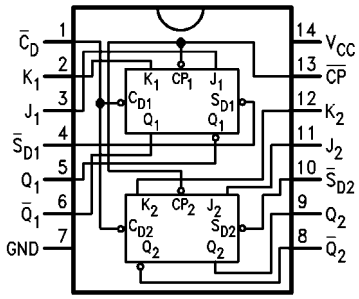
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
J_1, J_2, K_1, K_2	Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{CP}$	Clock Pulse Input (Active Falling Edge)	1.0/8.0	20 μA/–4.8 mA
$\overline{C}_D$	Direct Clear Input (Active LOW)	1.0/10.0	20 μA/–6.0 mA
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs (Active LOW)	1.0/5.0	20 μA/–3.0 mA
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs	50/33.3	–1 mA/20 mA

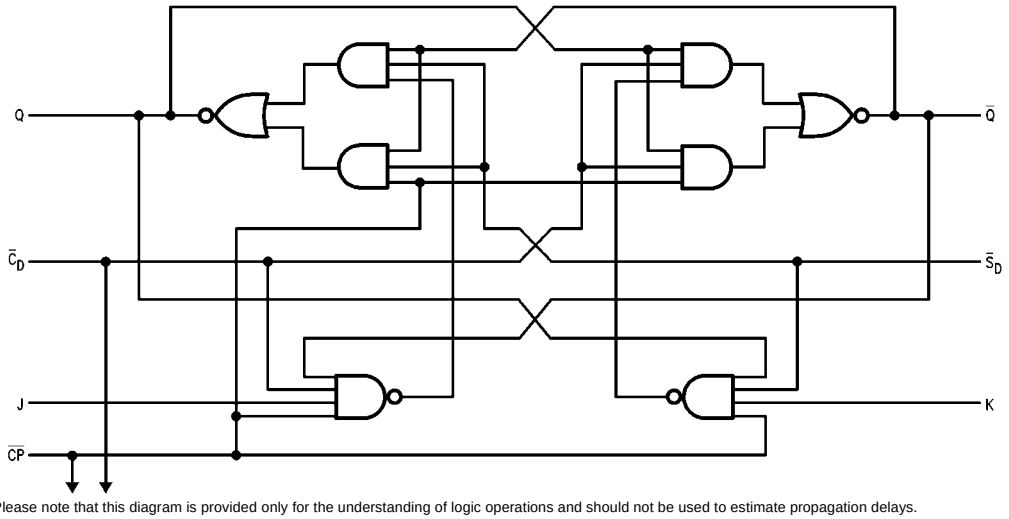
Truth Table

Inputs					Outputs	
$\overline{S}_D$	$\overline{C}_D$	$\overline{CP}$	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	h	h	$\overline{Q}_0$	Q_0
H	H	⌐	l	h	L	H
H	H	⌐	h	l	H	L
H	H	⌐	l	l	Q_0	$\overline{Q}_0$

H (h) = HIGH Voltage Level
L (h) = LOW Voltage Level
X = Immaterial
⌐ = HIGH-to-LOW Clock Transition
Q_0 ($\overline{Q}_0$) = Before HIGH-to-LOW Transition of Clock
Lower case letters indicate the state of the referenced input or output one setup time prior to the HIGH-to-LOW clock transition.

Logic Diagram

(one half shown)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output High Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (J_n, K_n)
					−3.0			V_{IN} = 0.5V ($\overline{S}_{Dn}$)
					−4.8			V_{IN} = 0.5V ($C\overline{P}$)
					−6.0			V_{IN} = 0.5V ($\overline{C}_{Dn}$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			12.0	19.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			12.0	19.0	mA	Max	V_O = LOW

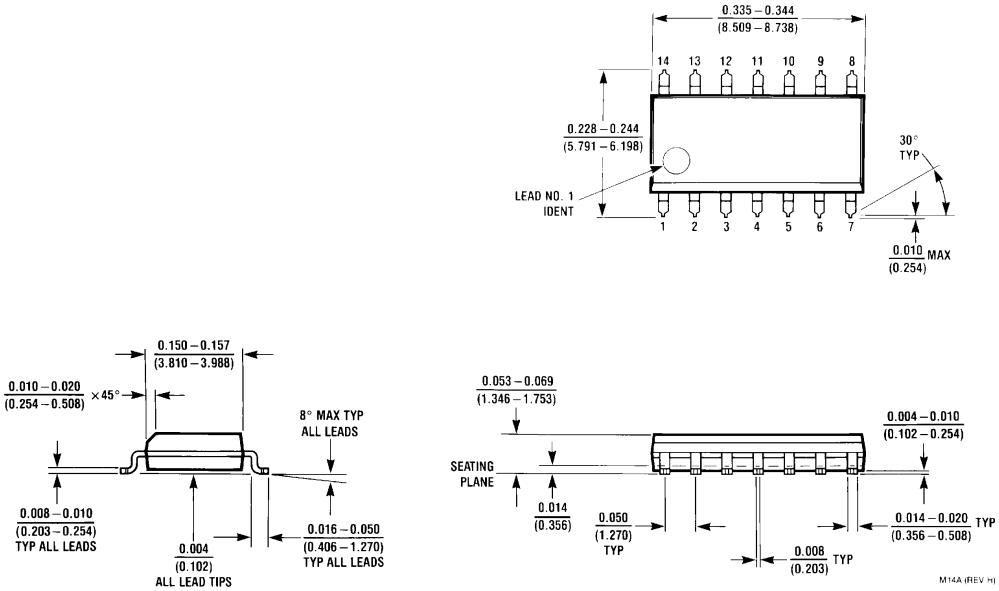
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	75	95		70		MHz
t_{PLH}	Propagation Delay	3.0	5.0	6.5	3.0	7.5	ns
t_{PHL}	$\overline{CP}$ to Q_n or $\overline{Q}_n$	3.0	5.5	7.5	3.0	8.5	
t_{PLH}	Propagation Delay	3.0	4.5	6.5	3.0	7.5	ns
t_{PHL}	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.0	4.5	6.5	3.0	7.5	

AC Operating Requirements

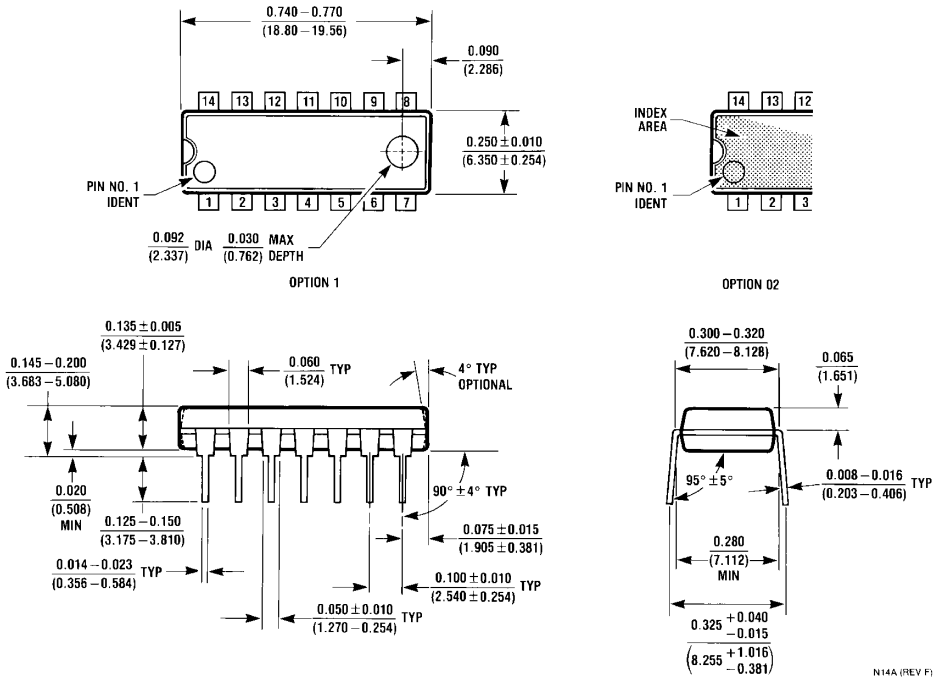
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		5.0		ns
$t_S(L)$	J_n or K_n to $\overline{CP}$	3.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		ns
$t_H(L)$	J_n or K_n to $\overline{CP}$	0		0		
$t_W(H)$	$\overline{CP}$ Pulse Width	4.5		5.0		ns
$t_W(L)$	HIGH or LOW	4.5		5.0		
$t_W(L)$	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ Pulse Width, LOW	4.5		5.0		ns
t_{REC}	Recovery Time $\overline{S}_{Dn}$, $\overline{C}_{Dn}$, to $\overline{CP}$	4.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F125
Quad Buffer (3-STATE)

Features

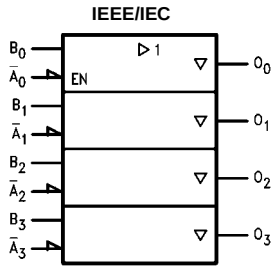
■ High impedance base inputs for reduced loading

Ordering Code:

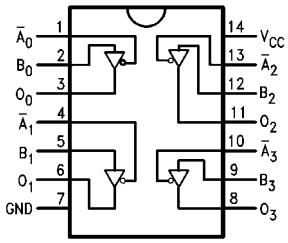
Order Number	Package Number	Package Description
74F125SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F125PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{A}_n$, B_n	Inputs	1.0/0.033	20 µA/–20 µA
O_n	Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Function Table

Inputs		Output
$\overline{A}_n$	B_n	O
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

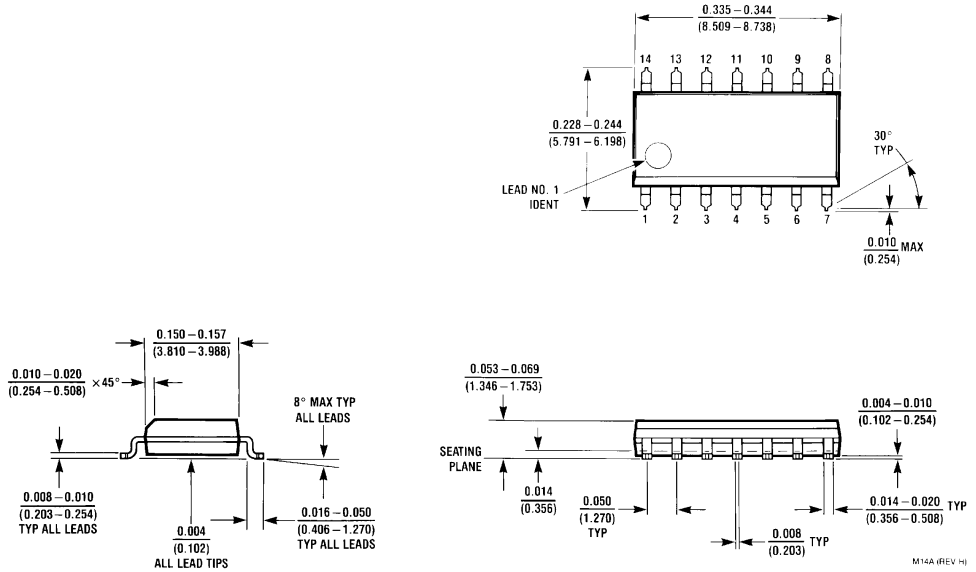
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		10% V_{CC}	2.0					I_{OH} = −12 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
		5% V_{CC}	2.0					I_{OH} = −15 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				20	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	0.0V	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−20.0	µA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Buss Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			18.5	24.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			31.7	40.0	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			27.6	35.0	mA	Max	V_O = HIGH Z

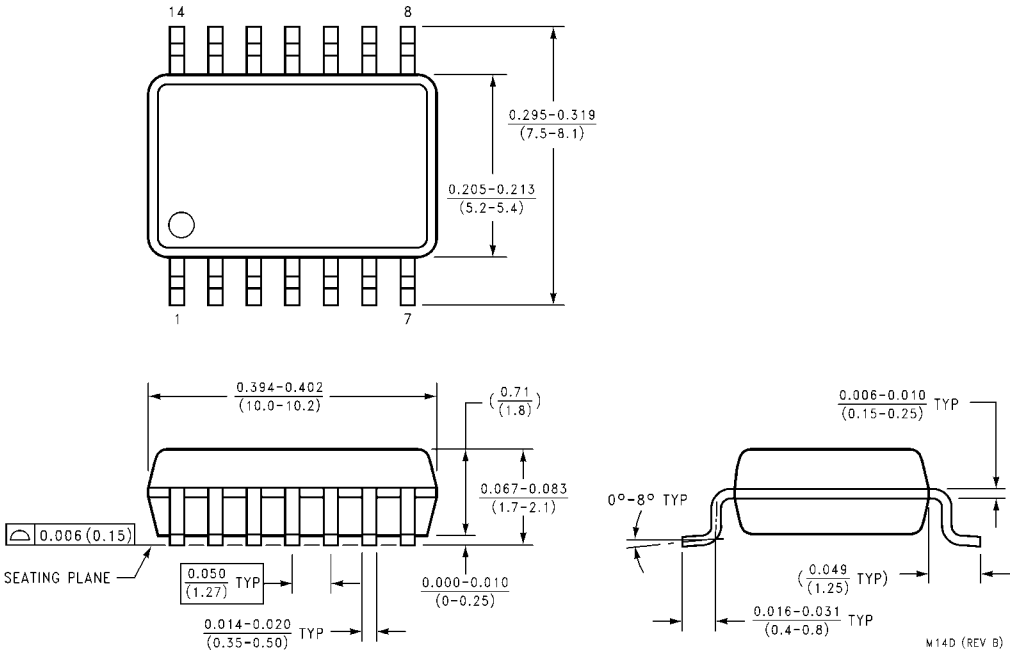
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.0	4.0	6.0	2.0	6.5	ns
t_{PHL}		3.0	4.6	7.5	3.0	8.0	
t_{PZH}	Output Enable Time	3.5	4.7	7.5	3.0	8.5	ns
t_{PZL}		3.5	5.3	8.0	3.5	9.0	
t_{PHZ}	Output Disable Time	1.5	3.9	5.5	1.5	6.0	ns
t_{PLZ}		1.5	4.0	6.0	1.5	6.5	

Physical Dimensions inches (millimeters) unless otherwise noted

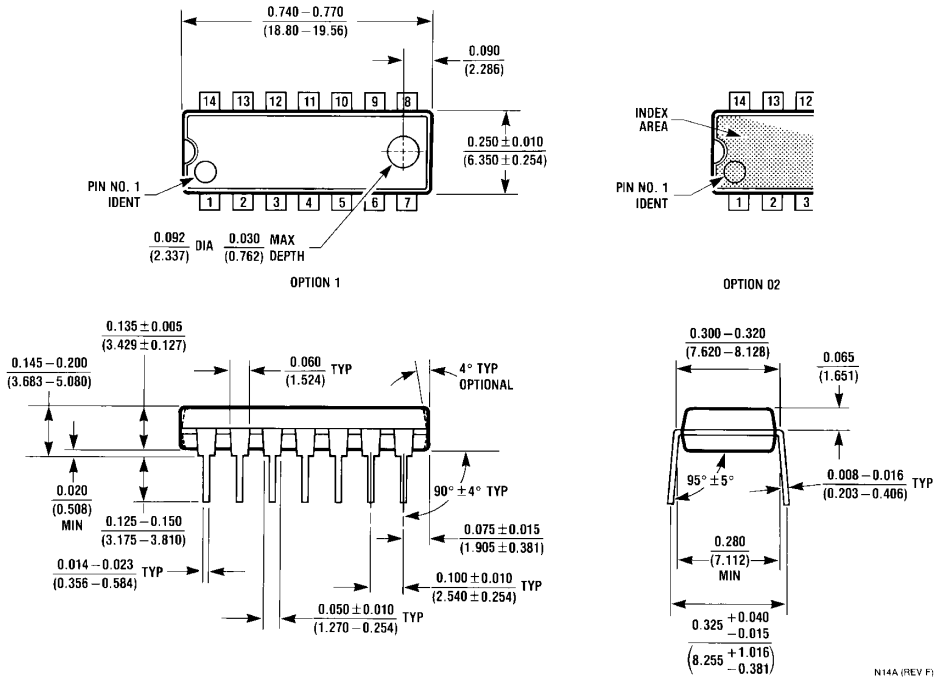


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F132
Quad 2-Input NAND Schmitt Trigger

General Description

The F132 contains four 2-input NAND gates which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional NAND gates.

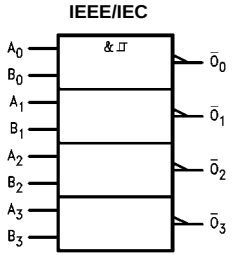
Each circuit contains a 2-input Schmitt Trigger followed by level shifting circuitry and a standard FAST™ output structure. The Schmitt Trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input threshold (typically 800 mV) is determined by resistor ratios and is essentially insensitive to temperature and supply voltage variations.

Ordering Code:

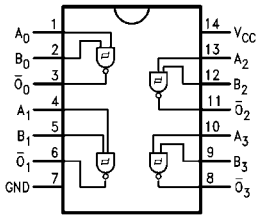
Order Number	Package Number	Package Description
74F132SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F132SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F132PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Function Table

Inputs		Outputs
A	B	$\overline{O}$
L	L	H
L	H	H
H	L	H
H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level

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Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

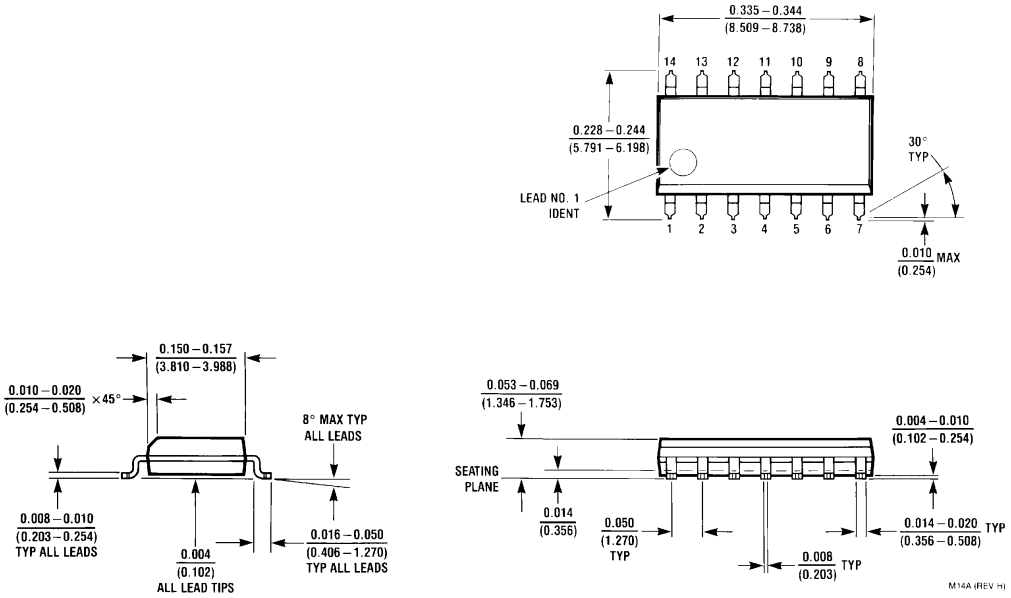
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{T+}	Positive-going Threshold		1.5		2.0	V	5.0	
V_{T-}	Negative-going Threshold		0.7		1.1	V	5.0	
ΔV_T	Hysteresis ($V_T^+ - V_T^-$)		0.4			V	5.0	
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	μA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	μA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current				17.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current				18.0	mA	Max	V_O = LOW

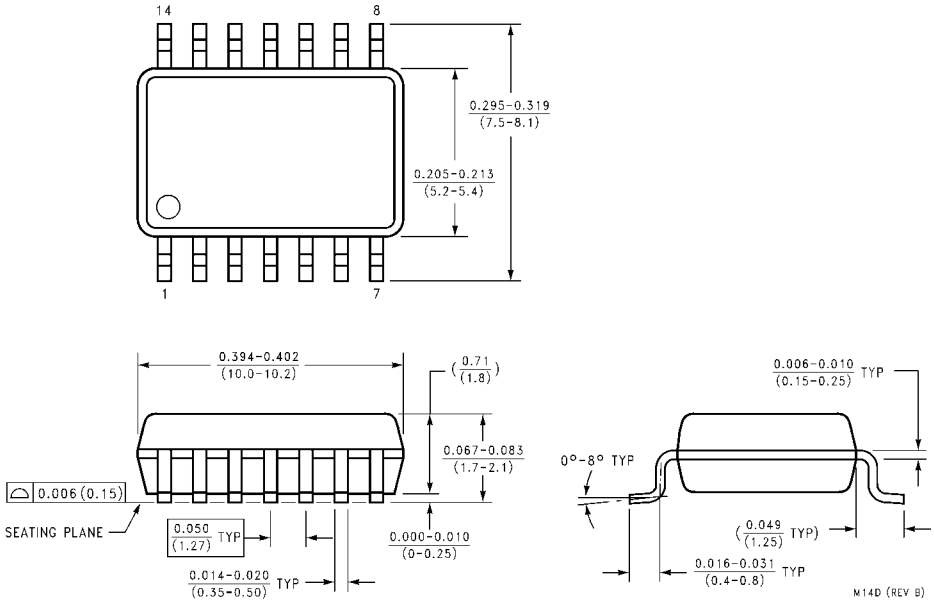
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0		10.5	3.5	12.0	ns
t_{PHL}	A_n, B_n to $\overline{O}_n$	5.0		12.5	5.0	13.0	

Physical Dimensions inches (millimeters) unless otherwise noted

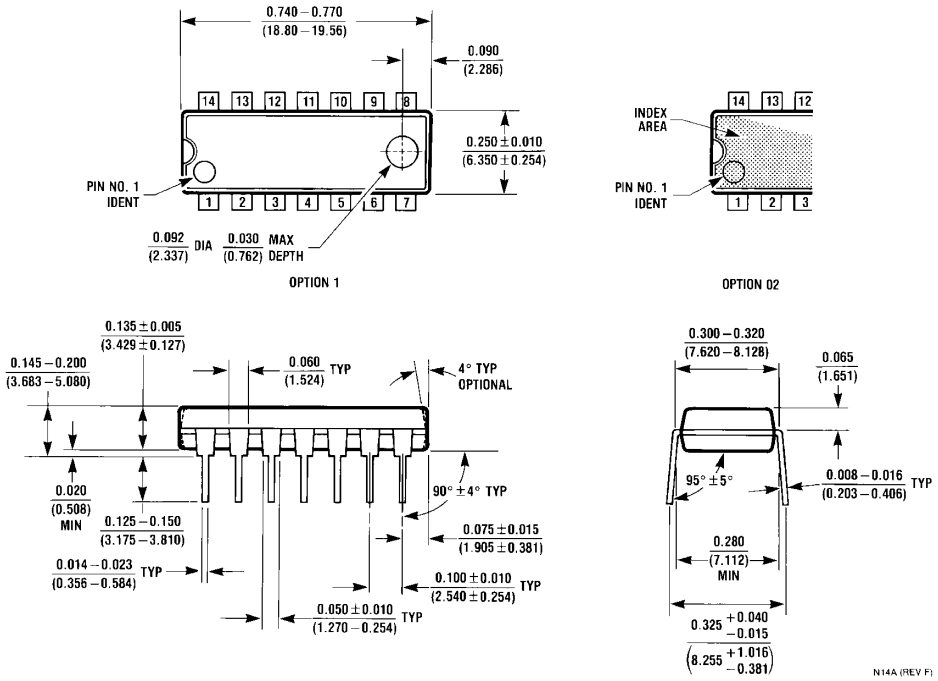


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F138
1-of-8 Decoder/Demultiplexer

General Description

The F138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed bipolar memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three F138 devices or a 1-of-32 decoder using four F138 devices and one inverter.

Features

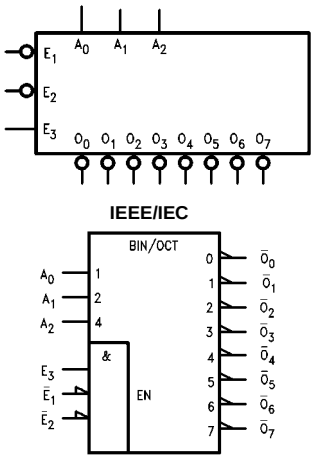
- Demultiplexing capability
- Multiple input enable for easy expansion
- Active LOW mutually exclusive outputs

Ordering Code:

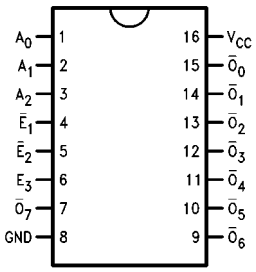
Order Number	Package Number	Package Description
74F138SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F138PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_2	Address Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{E}_1$, $\overline{E}_2$	Enable Inputs (Active LOW)	1.0/1.0	20 µA/–0.6 mA
E_3	Enable Input (Active HIGH)	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_0$–$\overline{O}_7$	Outputs (Active LOW)	50/33.3	–1 mA/20 mA

Truth Table

Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Description

The F138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A_0, A_1, A_2) and, when enabled, provides eight mutually exclusive active LOW outputs ($\overline{O}_0$–$\overline{O}_7$). The F138 features three Enable inputs, two active LOW ($\overline{E}_1$, $\overline{E}_2$) and one active HIGH (E_3). All outputs will be HIGH unless $\overline{E}_1$ and $\overline{E}_2$ are LOW and E_3 is HIGH. This multiple enable function allows easy parallel expansion of the device to a 1-of-32 (5 lines to 32 lines) decoder with just four F138 devices and one inverter (See Figure 1). The F138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active HIGH or active LOW state.

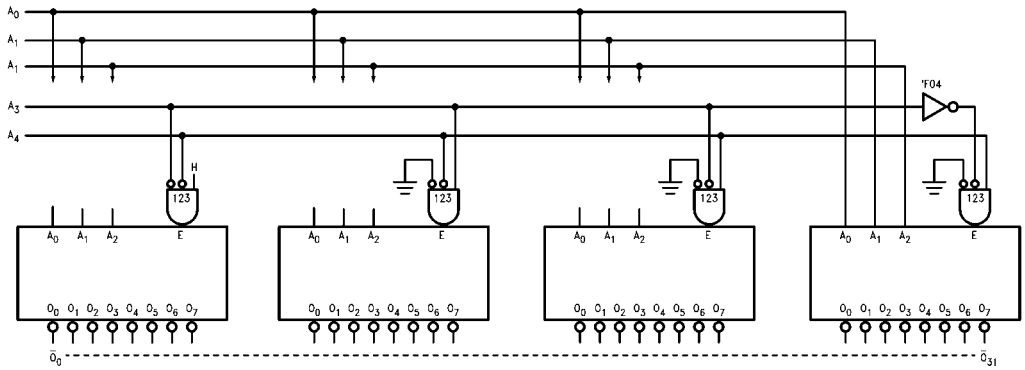
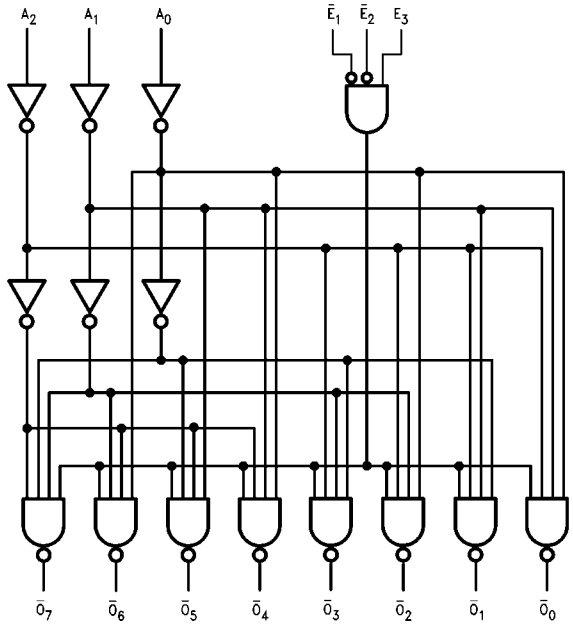


FIGURE 1. Expansion to 1-of-32 Decoding

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

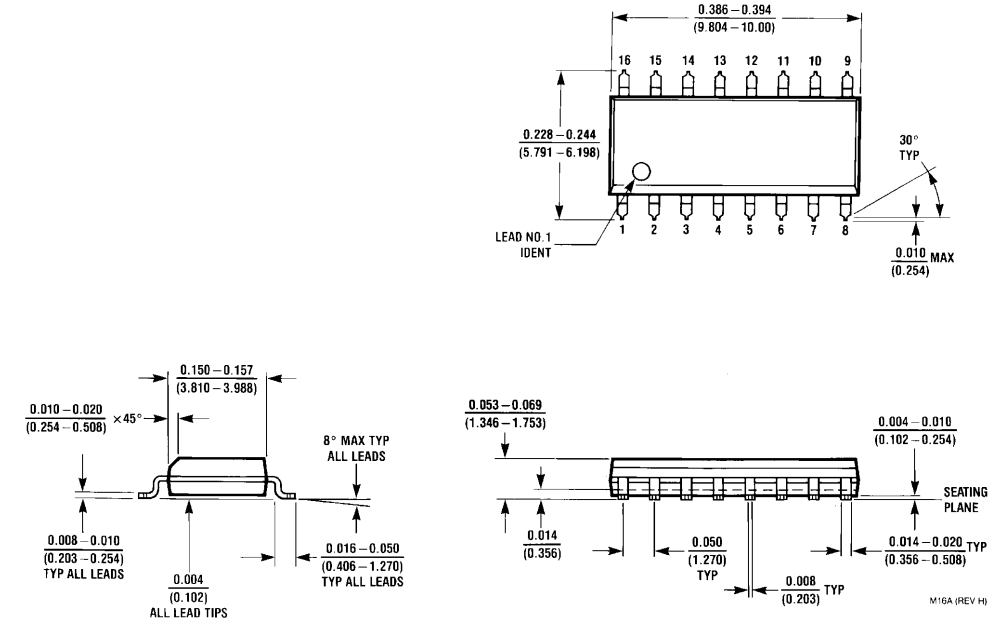
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			13	20	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			13	20	mA	Max	V_O = LOW

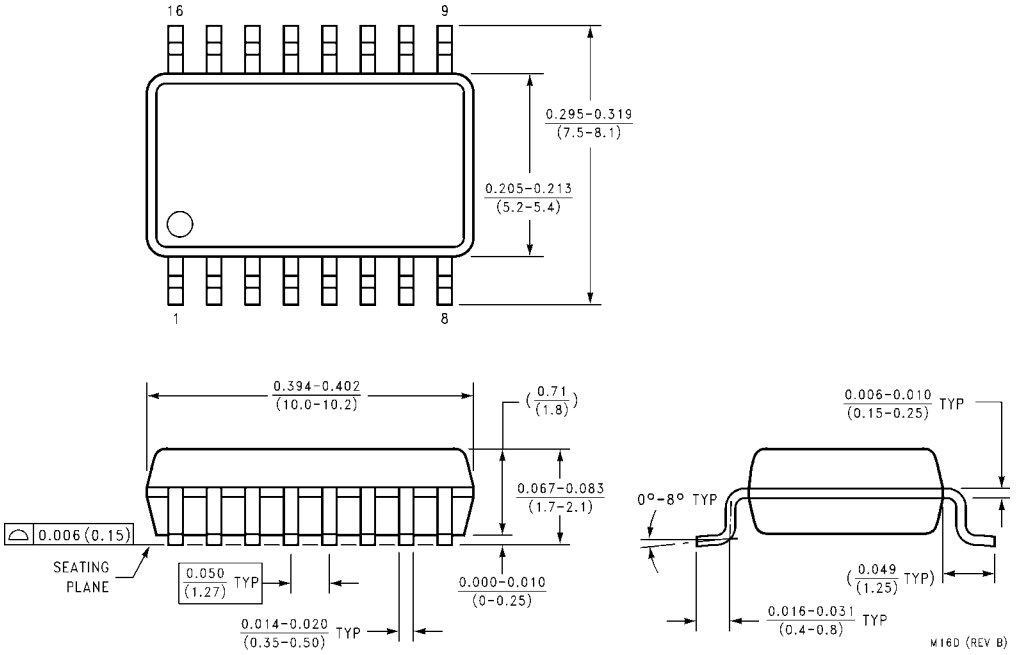
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.5	5.6	7.5	3.5	8.5	ns
t_{PHL}	A_n to $\overline{O}_n$	4.0	6.1	8.0	4.0	9.0	
t_{PLH}	Propagation Delay	3.5	5.4	7.0	3.5	8.0	ns
t_{PHL}	$\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	3.0	5.3	7.0	3.0	7.5	
t_{PLH}	Propagation Delay	4.0	6.2	8.0	4.0	9.0	ns
t_{PHL}	E_3 to $\overline{O}_n$	3.5	5.6	7.5	3.5	8.5	

Physical Dimensions inches (millimeters) unless otherwise noted

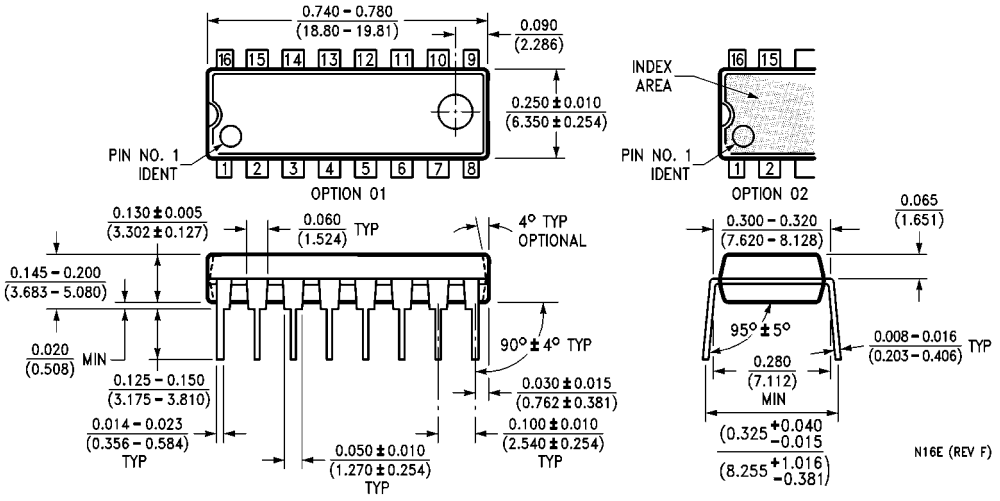


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F139
Dual 1-of-4 Decoder/Demultiplexer

General Description

The F139 is a high-speed, dual 1-of-4 decoder/demultiplexer. The device has two independent decoders, each accepting two inputs and providing four mutually exclusive active LOW outputs. Each decoder has an active LOW Enable input which can be used as a data input for a 4-output demultiplexer. Each half of the F139 can be used as a function generator providing all four minterms of two variables.

Features

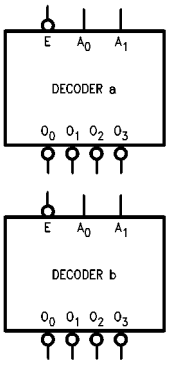
- Multifunction capability
- Two completely independent 1-of-4 decoders
- Active LOW mutually exclusive outputs

Ordering Code:

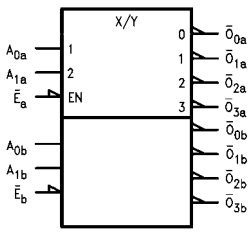
Order Number	Package Number	Package Description
74F139SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F139SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F139PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

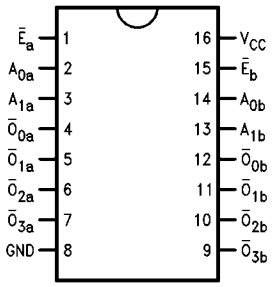
Logic Symbols



IEEE/IEC



Connection Diagram



Truth Table

Inputs			Outputs			
$\overline{E}$	A_0	A_1	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	H	L	H	L	H	H
L	L	H	H	H	L	H
L	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0, A_1	Address Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{E}$	Enable Inputs (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_0$–$\overline{O}_3$	Outputs (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The F139 is a high-speed dual 1-of-4 decoder/demultiplexer. The device has two independent decoders, each of which accepts two binary weighted inputs (A_0–A_1) and provides four mutually exclusive active LOW Outputs ($\overline{O}_0$–$\overline{O}_3$). Each decoder has an active LOW enable ($\overline{E}$). When $\overline{E}$ is HIGH all outputs are forced HIGH. The enable can be used as the data input for a 4-output demultiplexer application. Each half of the F139 generates all four minterms of two variables. These four minterms are useful in some applications, replacing multiple gate functions as shown in Figure 1, and thereby reducing the number of packages required in a logic network.

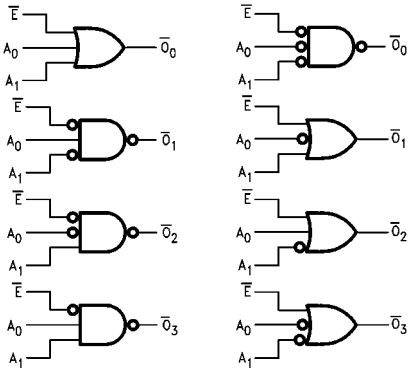
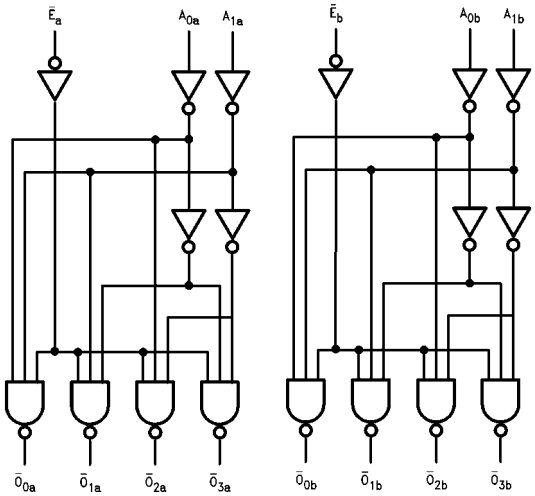


FIGURE 1. Gate Functions (each half)

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	–65°C to +150°C
Ambient Temperature under Bias	–55°C to +125°C
Junction Temperature under Bias	–55°C to +150°C
V_{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
Input Voltage (Note 2)	–0.5V to +7.0V
Input Current (Note 2)	–30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	–0.5V to V_{CC}
3 STATE Output	–0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

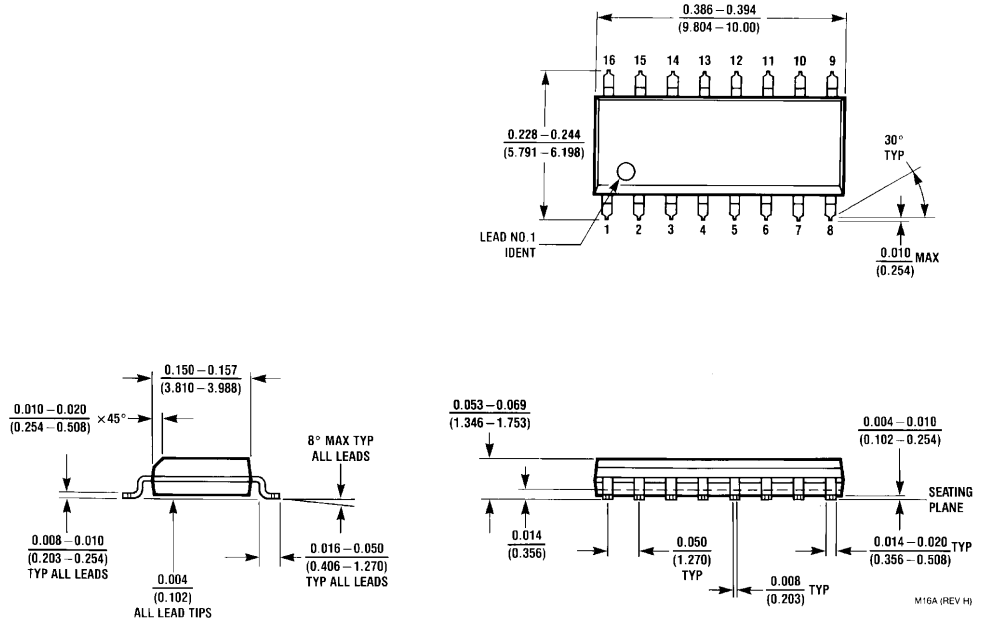
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				–1.2	V	Min	I_{IN} = –18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = –1 mA
		5% V_{CC}	2.7					I_{OH} = –1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				–0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		–60		–150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			13	20	mA	Max	

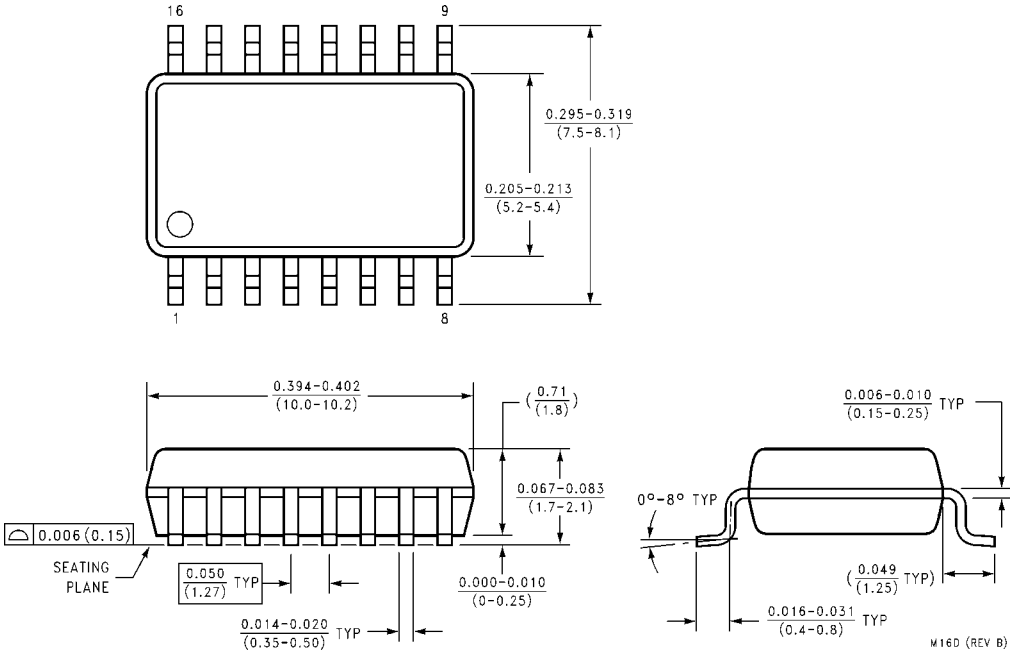
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.5	5.3	7.5	3.0	8.5	ns
t_{PHL}	A_0 or A_1 to $\overline{O}_n$	4.0	6.1	8.0	4.0	9.0	
t_{PLH}	Propagation Delay	3.5	5.4	7.0	3.5	8.0	ns
t_{PHL}	$\overline{E}_1$ to $\overline{O}_n$	3.0	4.7	6.5	3.0	7.5	

Physical Dimensions inches (millimeters) unless otherwise noted

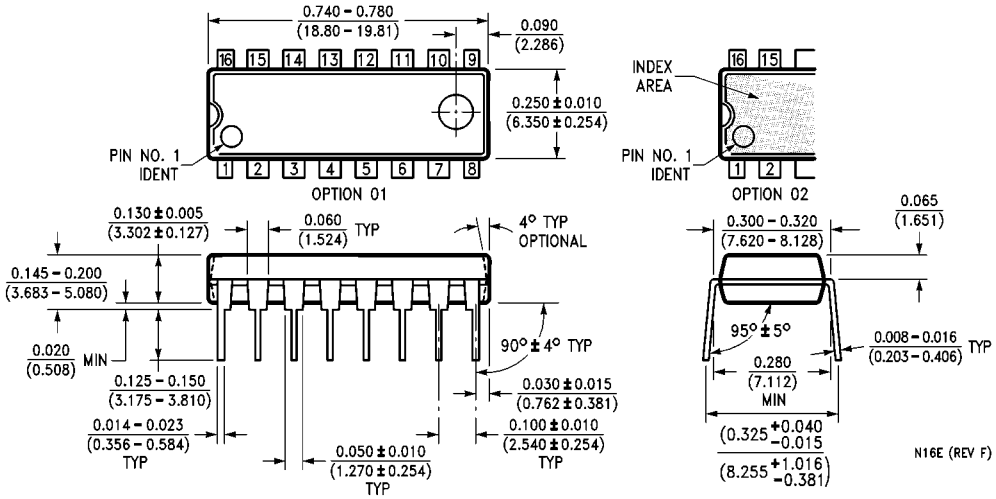


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

March 1988
Revised July 1999

74F14
Hex Inverter Schmitt Trigger

General Description

The 74F14 contains six logic inverters which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

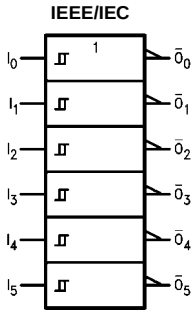
Each circuit contains a Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem-pole output. The Schmitt trigger uses positive feed back to effectively speed-up slow input transition, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input thresholds (typically 800 mV) is determined internally by resistor ratios and is essentially insensitive to temperature and supply voltage variations.

Ordering Code:

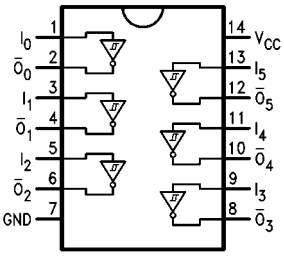
Order Number	Package Number	Package Description
74F14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F14PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_n	Input	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_n$	Output	50/33.3	–1 mA/20 mA

Function Table

Input	Output
A	$\overline{O}$
L	H
H	L

H = HIGH Voltage Level
L = LOW Voltage Level

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

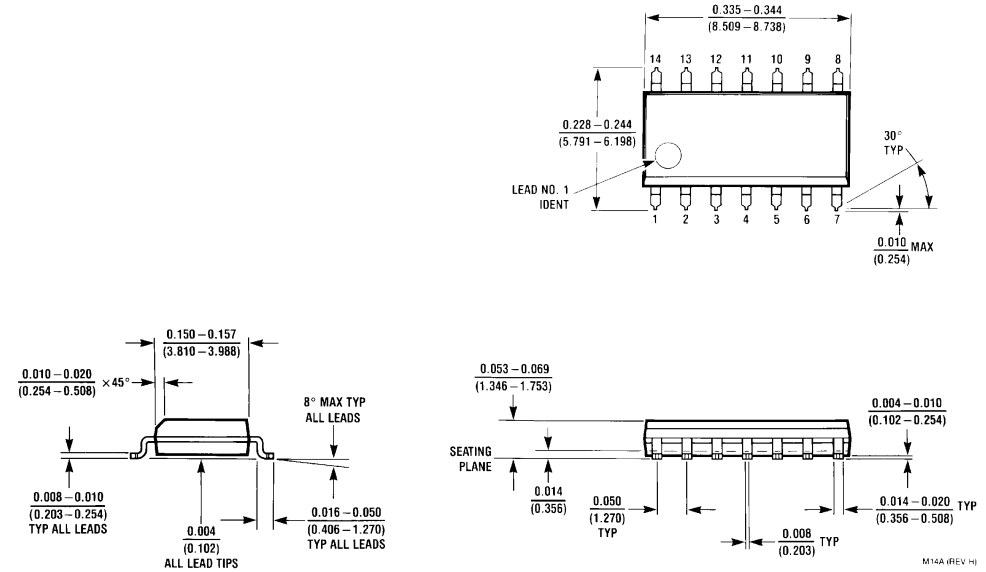
DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{T+}	Positive-Going Threshold	1.5	1.7	2.0	V	5.0V	
V_{T-}	Negative-Going Threshold	0.7	0.9	1.1	V	5.0V	
ΔV_T	Hysteresis (V_{T+}–V_{T-})	0.4	0.8		V	5.0V	
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	Max	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			25	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			25	mA	Max	V_O = LOW

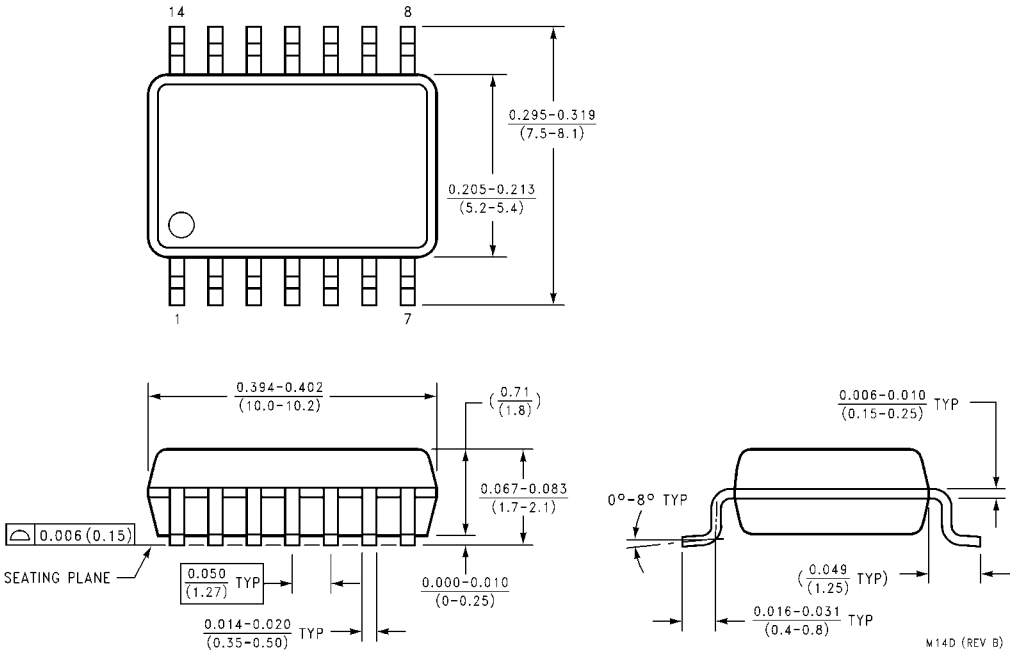
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0	10.5	4.0	13.0	4.0	11.5	ns
t_{PHL}	$I_n \rightarrow \overline{O}_n$	3.5	8.5	3.5	10.0	3.5	9.0	

Physical Dimensions inches (millimeters) unless otherwise noted

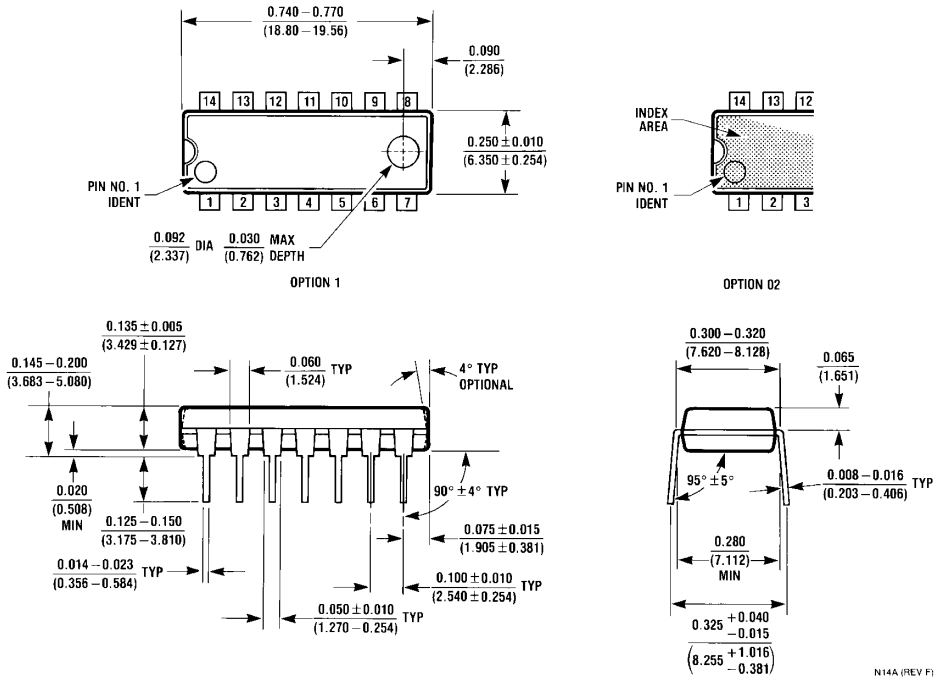


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F148
8-Line to 3-Line Priority Encoder

General Description

The F148 provides three bits of binary coded output representing the position of the highest order active input, along with an output indicating the presence of any active input. It is easily expanded via input and output enables to provide priority encoding over many bits.

Features

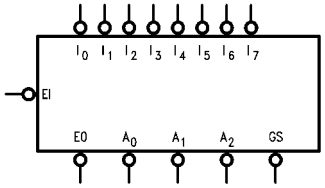
- Encodes eight data lines in priority
- Provides 3-bit binary priority code
- Input enable capability
- Signals when data is present on any input
- Cascadable for priority encoding of n bits

Ordering Code:

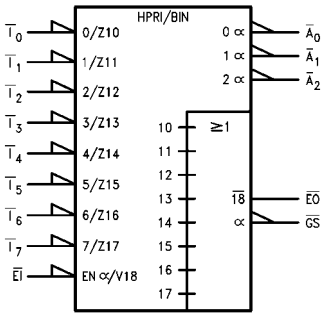
Order Number	Package Number	Package Description
74F148SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F148SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F148PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

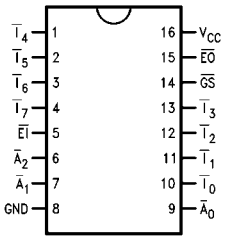
Logic Symbols



IEEE/IEC



Connection Diagram



Truth Table

Inputs									Outputs				
$\overline{EI}$	$\overline{I_0}$	$\overline{I_1}$	$\overline{I_2}$	$\overline{I_3}$	$\overline{I_4}$	$\overline{I_5}$	$\overline{I_6}$	$\overline{I_7}$	$\overline{GS}$	$\overline{A_0}$	$\overline{A_1}$	$\overline{A_2}$	$\overline{EO}$
H	X	X	X	X	X	X	X	X	H	H	H	H	H
L	H	H	H	H	H	H	H	H	H	H	H	H	L
L	X	X	X	X	X	X	X	L	L	L	L	L	H
L	X	X	X	X	X	X	L	H	L	H	L	L	H
L	X	X	X	X	X	L	H	H	L	L	H	L	H
L	X	X	X	X	L	H	H	H	L	H	H	L	H
L	X	X	X	L	H	H	H	H	L	L	L	H	H
L	X	X	L	H	H	H	H	H	L	H	L	H	H
L	X	L	H	H	H	H	H	H	L	L	H	H	H
L	L	H	H	H	H	H	H	H	L	H	H	H	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

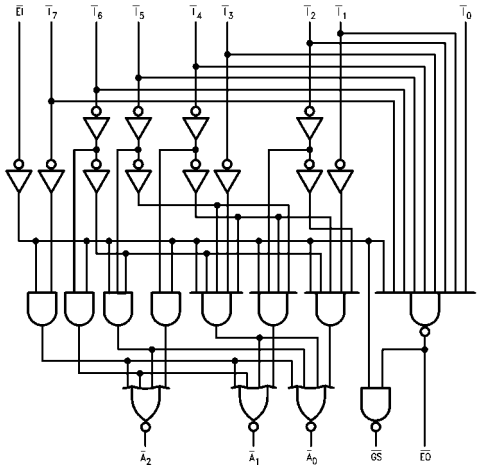
Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{I}_0$	Priority Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{I}_1$–$\overline{I}_7$	Priority Inputs (Active LOW)	1.0/2.0	20 μA/–1.2 mA
$\overline{EI}$	Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{EO}$	Enable Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{GS}$	Group Signal Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{A}_0$–$\overline{A}_2$	Address Outputs (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The F148 8-input priority encoder accepts data from eight active LOW inputs ($\overline{I}_0$–$\overline{I}_7$) and provides a binary representation on the three active LOW outputs. A priority is assigned to each input so that when two or more inputs are simultaneously active, the input with the highest priority is represented on the output, with input line 7 having the highest priority. A HIGH on the Enable Input ($\overline{EI}$) will force all outputs to the inactive (HIGH) state and allow new data to settle without producing erroneous information at the outputs.A Group Signal output ($\overline{GS}$) and Enable Output ($\overline{EO}$) are provided along with the three priority data outputs ($\overline{A}_2$, $\overline{A}_1$, $\overline{A}_0$). $\overline{GS}$ is active LOW when any input is LOW: this indicates when any input is active. $\overline{EO}$ is active LOW when all inputs are HIGH. Using the Enable Output along with the Enable Input allows cascading for priority encoding on any number of input signals. Both $\overline{EO}$ and $\overline{GS}$ are in the inactive HIGH state when the Enable Input is HIGH.

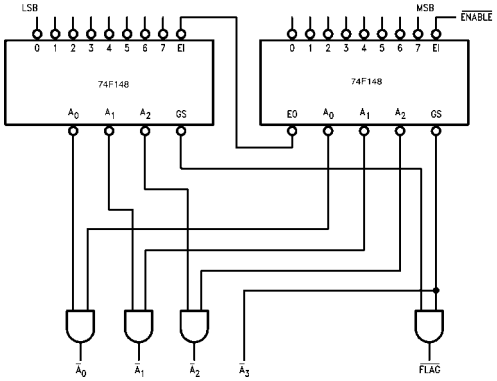
Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Application

16-Input Priority Encoder



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

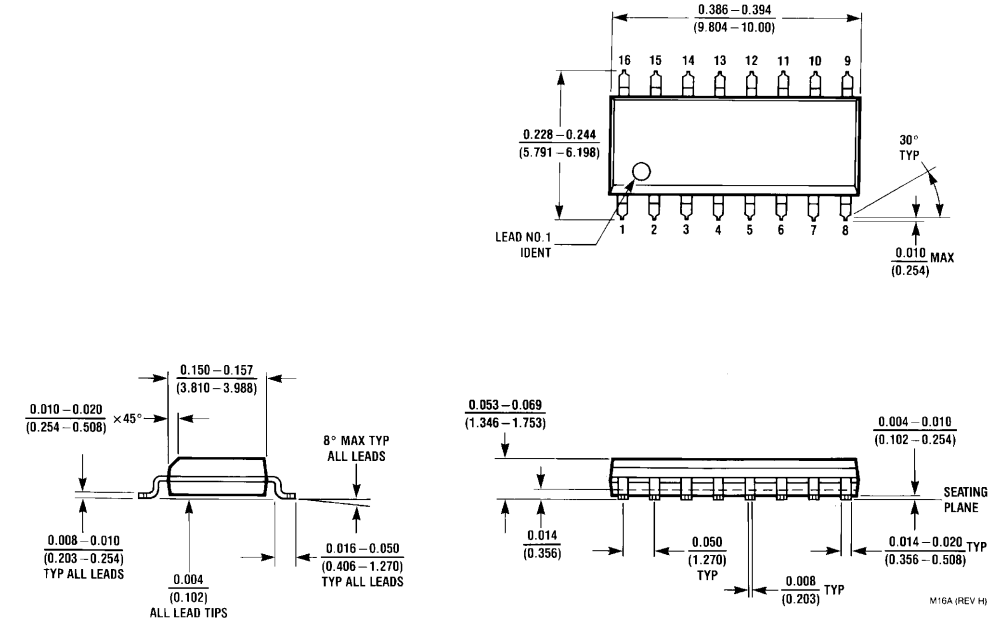
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output High Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V ($\bar{I}_0$, $\overline{EI}$)
					−1.2	mA		V_{IN} = 0.5V ($\bar{I}_1$–$\bar{I}_7$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current				35	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current				35	mA	Max	V_O = LOW

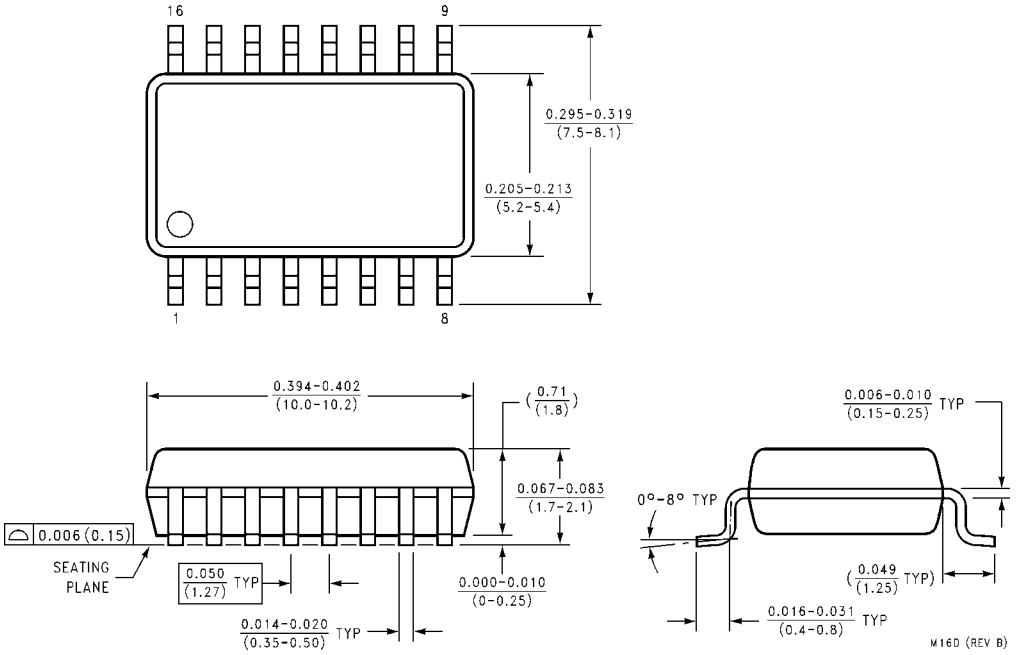
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	7.0	9.0	3.0	10.0	ns
t_{PHL}	$\overline{I}_n$ to $\overline{A}_n$	3.0	8.0	10.5	3.0	12.0	
t_{PLH}	Propagation Delay	2.5	5.0	6.5	2.5	7.5	ns
t_{PHL}	$\overline{I}_n$ to $\overline{EO}$	2.5	5.5	7.5	2.5	8.5	
t_{PLH}	Propagation Delay	2.5	7.0	9.0	2.5	10.0	ns
t_{PHL}	$\overline{I}_n$ to $\overline{GS}$	2.5	6.0	8.0	2.5	9.0	
t_{PLH}	Propagation Delay	2.5	6.5	8.5	2.5	9.5	ns
t_{PHL}	$\overline{EI}$ to $\overline{A}_n$	2.5	6.0	8.0	2.5	9.0	
t_{PLH}	Propagation Delay	2.5	5.0	7.0	2.5	8.0	ns
t_{PHL}	$\overline{EI}$ to $\overline{GS}$	2.5	6.0	7.5	2.5	8.5	
t_{PLH}	Propagation Delay	2.5	5.5	7.0	2.5	8.0	ns
t_{PHL}	$\overline{EI}$ to $\overline{EO}$	3.0	8.0	10.5	3.0	12.0	

Physical Dimensions inches (millimeters) unless otherwise noted

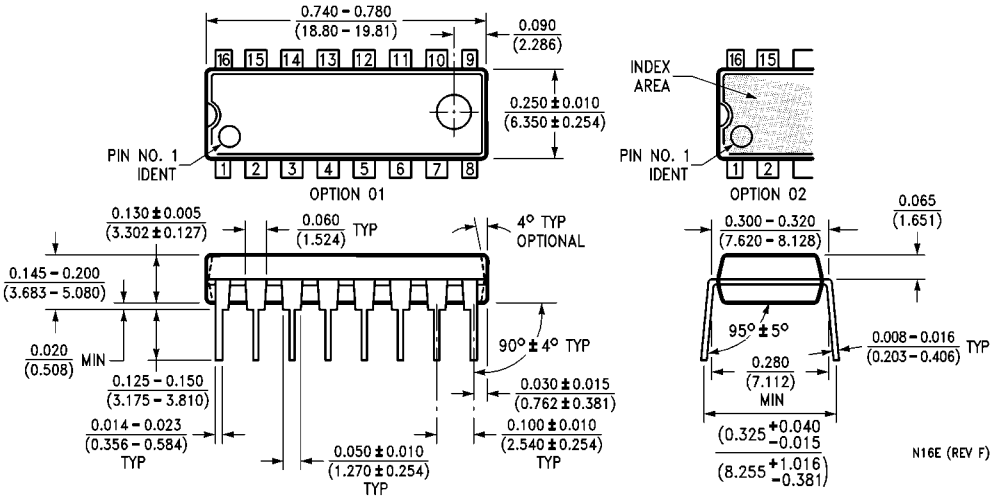


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised March 1999

74F151A
8-Input Multiplexer

General Description

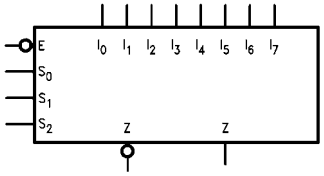
The F151A is a high-speed 8-input digital multiplexer. It provides in one package the ability to select one line of data from up to eight sources. The F151A can be used as a universal function generator to generate any logic function of four variables. Both assertion and negation outputs are provided.

Ordering Code:

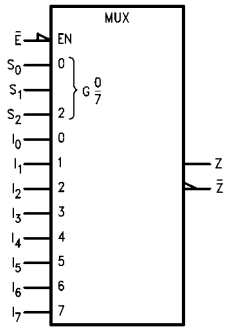
Order Number	Package Number	Package Description
74F151ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F151ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F151APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

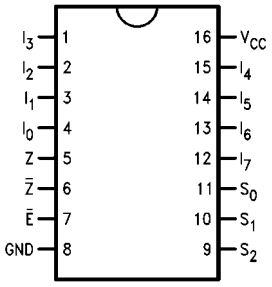
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_0–I_7	Data Inputs	1.0/1.0	20 µA/–0.6 mA
S_0–S_2	Select Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{E}$	Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
Z	Data Output	50/33.3	–1 mA/20 mA
$\overline{Z}$	Inverted Data Output	50/33.3	–1 mA/20 mA

Functional Description

The F151A is a logic implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0, S_1, S_2. Both assertion and negation outputs are provided. The Enable input ($\overline{E}$) is active LOW. When it is not activated, the negation output is HIGH and the assertion output is LOW regardless of all other inputs. The logic function provided at the output is:

$$Z = \overline{E} \bullet (I_0\,\overline{S}_2\,\overline{S}_1\,\overline{S}_0 + I_1\,\overline{S}_2\,\overline{S}_1\,S_0 + I_2\,\overline{S}_2\,S_1\,\overline{S}_0 + I_3\,\overline{S}_2\,S_1\,S_0 + I_4\,S_2\,\overline{S}_1\,\overline{S}_0 + I_5\,S_2\,\overline{S}_1\,S_0 + I_6\,S_2\,S_1\,\overline{S}_0 + I_7\,S_2\,S_1\,S_0)$$

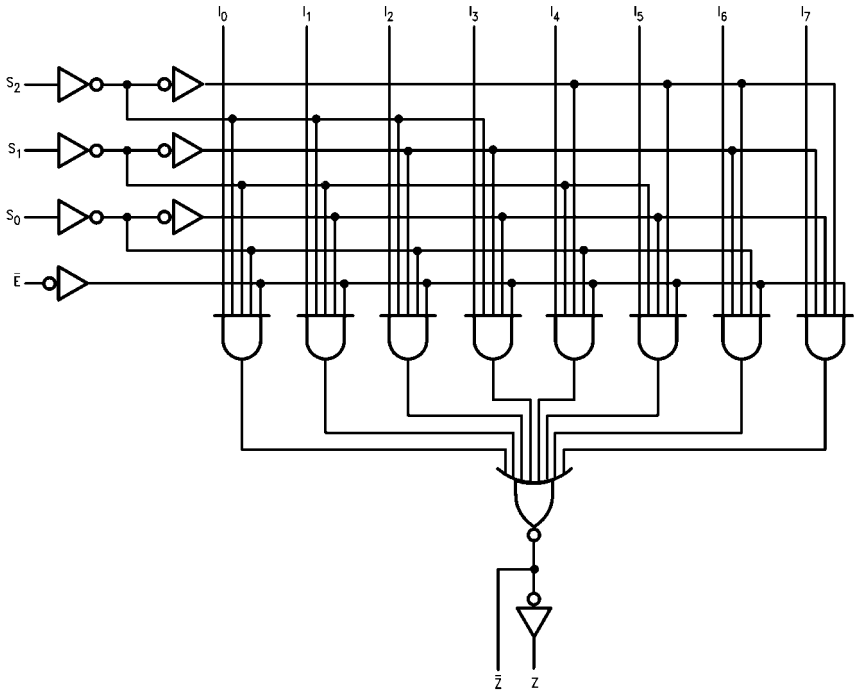
The F151A provides the ability, in one package, to select from eight sources of data or control information. By proper manipulation of the inputs, the F151A can provide any logic function of four variables and its negation.

Truth Table

Inputs				Outputs	
$\overline{E}$	S_2	S_1	S_0	$\overline{Z}$	Z
H	X	X	X	H	L
L	L	L	L	$\overline{I}_0$	I_0
L	L	L	H	$\overline{I}_1$	I_1
L	L	H	L	$\overline{I}_2$	I_2
L	L	H	H	$\overline{I}_3$	I_3
L	H	L	L	$\overline{I}_4$	I_4
L	H	L	H	$\overline{I}_5$	I_5
L	H	H	L	$\overline{I}_6$	I_6
L	H	H	H	$\overline{I}_7$	I_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

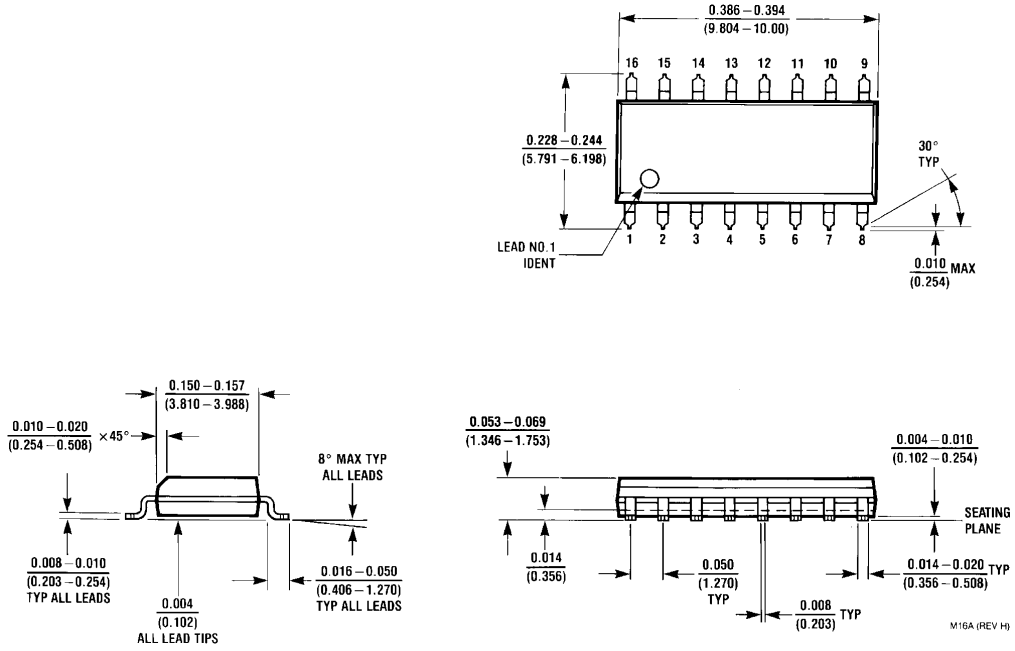
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			13.5	21.0	mA	Max	V_O = HIGH

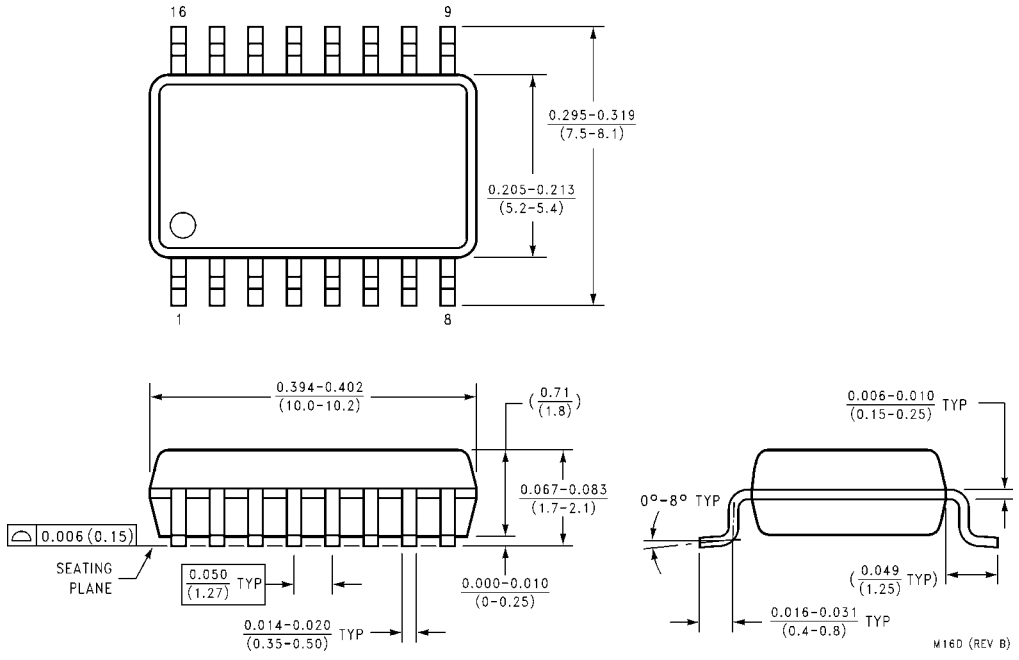
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0	6.2	9.0	3.5	9.5	ns
t_{PHL}	S_n to $\overline{Z}$	3.2	5.2	7.5	3.2	7.5	
t_{PLH}	Propagation Delay	4.5	7.5	10.5	4.5	12.0	ns
t_{PHL}	S_n to Z	4.0	6.2	9.0	4.0	9.0	
t_{PLH}	Propagation Delay	3.0	4.7	6.1	3.0	7.0	ns
t_{PHL}	$\overline{E}$ to $\overline{Z}$	3.0	4.4	6.0	2.5	6.0	
t_{PLH}	Propagation Delay	5.0	7.0	9.5	4.0	10.5	ns
t_{PHL}	$\overline{E}$ to Z	3.5	5.3	7.0	3.0	7.5	
t_{PLH}	Propagation Delay	3.0	4.8	6.5	3.0	7.0	ns
t_{PHL}	I_n to $\overline{Z}$	1.5	2.5	4.0	1.5	5.0	
t_{PLH}	Propagation Delay	3.0	4.8	6.5	2.5	7.5	ns
t_{PHL}	I_n to Z	3.7	5.5	7.0	3.7	7.5	

Physical Dimensions inches (millimeters) unless otherwise noted

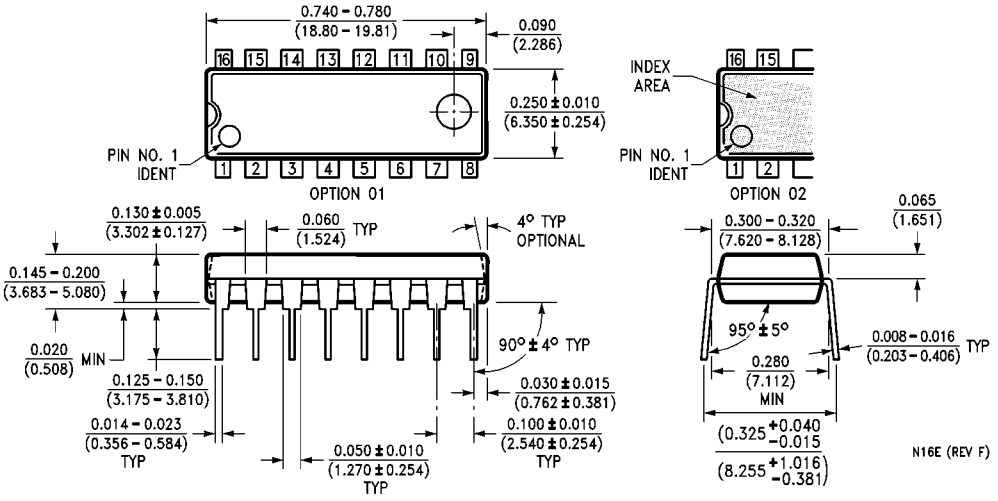


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F153
Dual 4-Input Multiplexer

General Description

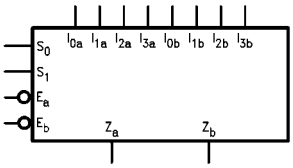
The F153 is a high-speed dual 4-input multiplexer with common select inputs and individual enable inputs for each section. It can select two lines of data from four sources. The two buffered outputs present data in the true (non-inverted) form. In addition to multiplexer operation, the F153 can generate any two functions of three variables.

Ordering Code:

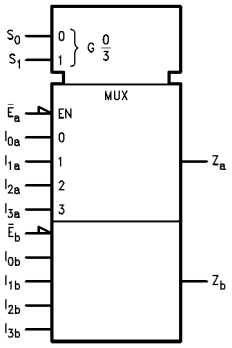
Order Number	Package Number	Package Description
74F153SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F153SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F153PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

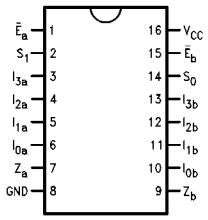
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_{0a}–I_{3a}	Side A Data Inputs	1.0/1.0	20 µA/–0.6 mA
I_{0b}–I_{3b}	Side B Data Inputs	1.0/1.0	20 µA/–0.6 mA
S_0, S_1	Common Select Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{E}_a$	Side A Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{E}_b$	Side B Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
Z_a	Side A Output	50/33.3	–1 mA/20 mA
Z_b	Side B Output	50/33.3	–1 mA/20 mA

Truth Table

Select Inputs		Inputs (a or b)					Output
S_0	S_1	$\overline{E}$	I_0	I_1	I_2	I_3	Z
X	X	H	X	X	X	X	L
L	L	L	L	X	X	X	L
L	L	L	H	X	X	X	H
H	L	L	X	L	X	X	L
H	L	L	X	H	X	X	H
L	H	L	X	X	L	X	L
L	H	L	X	X	H	X	H
H	H	L	X	X	X	L	L
H	H	L	X	X	X	H	H

H = HIGH Voltage Level
L = LOW
X = Immaterial

Functional Description

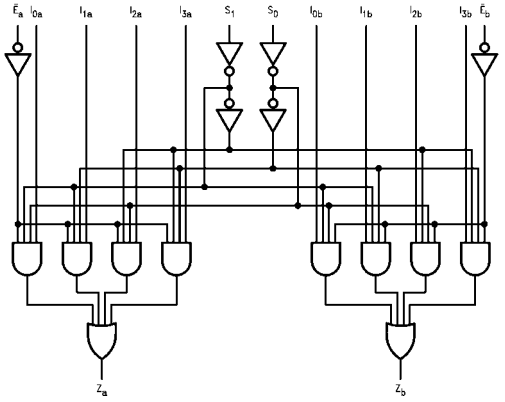
The F153 is a dual 4-input multiplexer. It can select two bits of data from up to four sources under the control of the common Select inputs (S_0, S_1). The two 4-input multiplexer circuits have individual active LOW Enables ($\overline{E}_a$, $\overline{E}_b$) which can be used to strobe the outputs independently. When the Enables ($\overline{E}_a$, $\overline{E}_b$) are HIGH, the corresponding outputs (Z_a, Z_b) are forced LOW. The F153 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two Select inputs. The logic equations for the outputs are as follows:

$$Z_a = \overline{E}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0)$$

$$Z_b = \overline{E}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet \overline{S}_0 + I_{3b} \bullet S_1 \bullet S_0)$$

The F153 can be used to move data from a group of registers to a common output bus. The particular register from which the data came would be determined by the state of the Select inputs. A less obvious application is as a function generator. The F153 can generate two functions of three variables. This is useful for implementing highly irregular random logic.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	–65°C to +150°C
Ambient Temperature under Bias	–55°C to +125°C
Junction Temperature under Bias	–55°C to +150°C
V_{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
Input Voltage (Note 2)	–0.5V to +7.0V
Input Current (Note 2)	–30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	–0.5V to V_{CC}
3-STATE Output	–0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

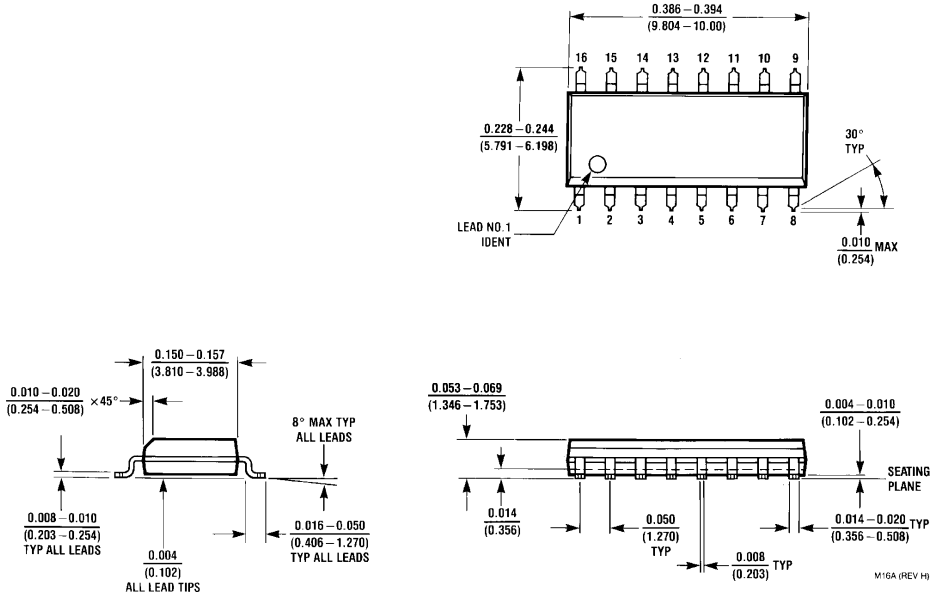
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				–1.2	V	Min	I_{IN} = –18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = –1 mA
		5% V_{CC}	2.7					I_{OH} = –1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output High Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				–0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		–60		–150	mA	Max	V_{OUT} = 0V
I_{CCL}	Power Supply Current			12	20	mA	Max	V_O = LOW

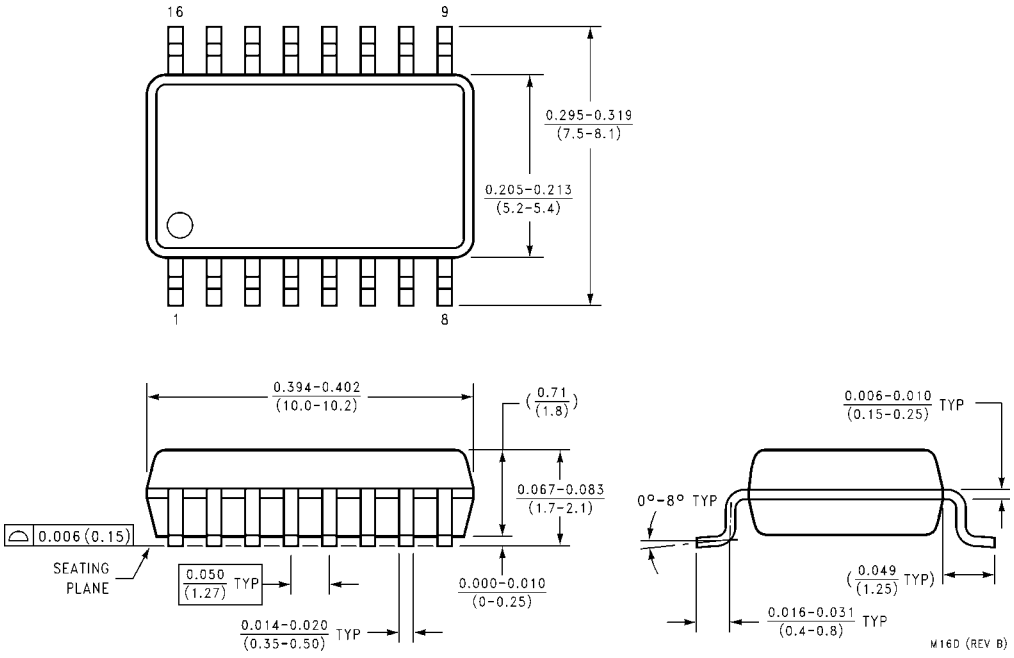
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.5	8.1	10.5	4.5	12.0	ns
t_{PHL}	S_n to Z_n	3.5	7.0	9.0	3.5	10.5	
t_{PLH}	Propagation Delay	4.5	7.1	9.0	4.5	10.5	ns
t_{PHL}	$\overline{E}_n$ to Z_n	3.0	5.7	7.0	2.5	8.0	
t_{PLH}	Propagation Delay	3.0	5.3	7.0	3.0	8.0	ns
t_{PHL}	I_n to Z_n	2.5	5.1	6.5	2.5	7.5	

Physical Dimensions inches (millimeters) unless otherwise noted

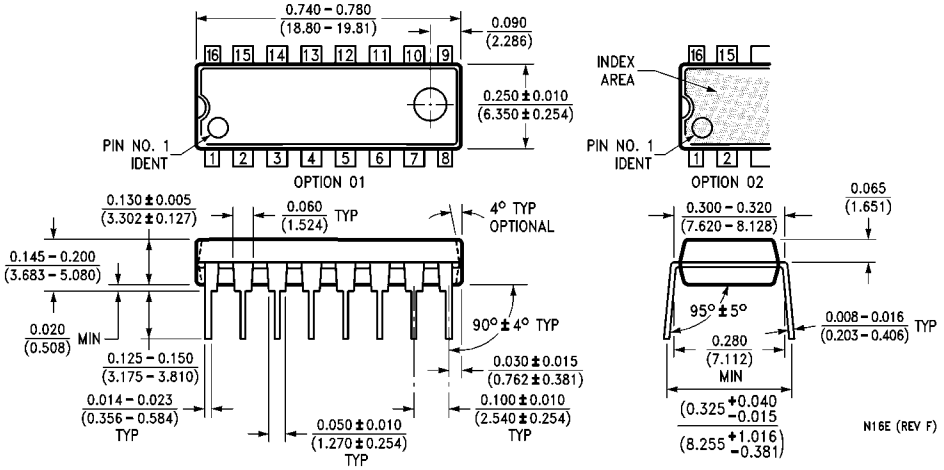


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F157A
Quad 2-Input Multiplexer

General Description

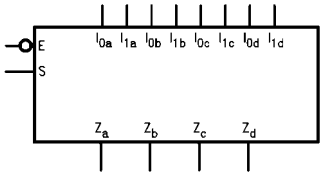
The F157A is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (non-inverted) form. The F157A can also be used to generate any four of the 16 different functions to two variables.

Ordering Code:

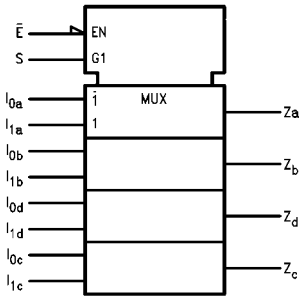
Order Number	Package Number	Package Description
74F157ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F157ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F157APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

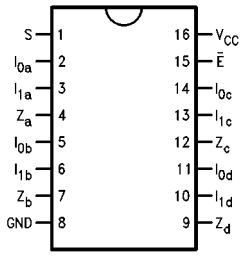
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_{0a}–I_{0d}	Source 0 Data Inputs	1.0/1.0	20 μA/–0.6 mA
I_{1a}–I_{1d}	Source 1 Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{E}$	Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
S	Select Input	1.0/1.0	20 μA/–0.6 mA
Z_a–Z_d	Outputs	50/33.3	–1 mA/20 mA

Truth Table

Inputs				Output
$\overline{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

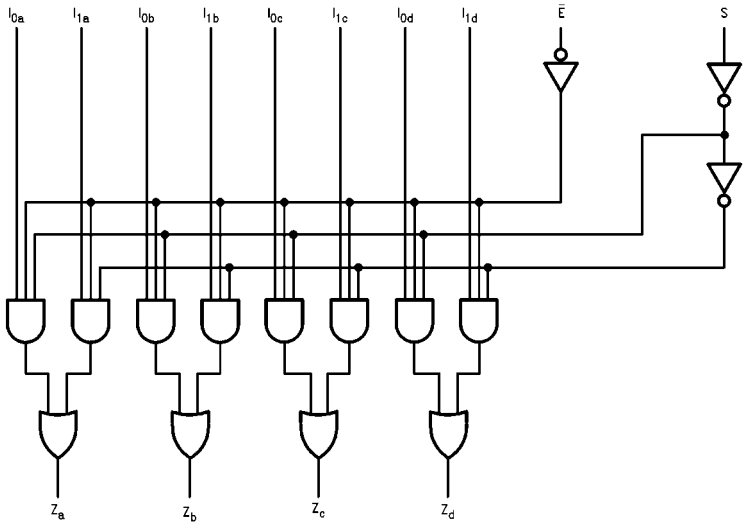
Functional Description

The F157A is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\overline{E}$) is active LOW. When $\overline{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The F157A is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$$Z_n = \overline{E} \bullet (I_{1n}S + I_{0n}\overline{S})$$

A common use of the F157A is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The F157A can generate any four of the 16 different functions of two variables with one variable common. This is useful for implementing highly irregular logic.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

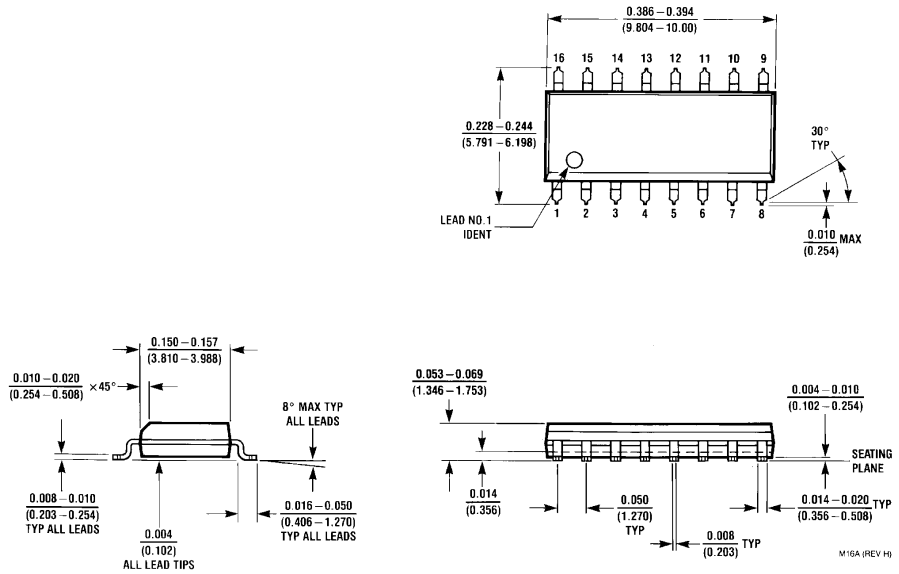
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW							
	Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			15	23	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			15	23	mA	Max	V_O = LOW

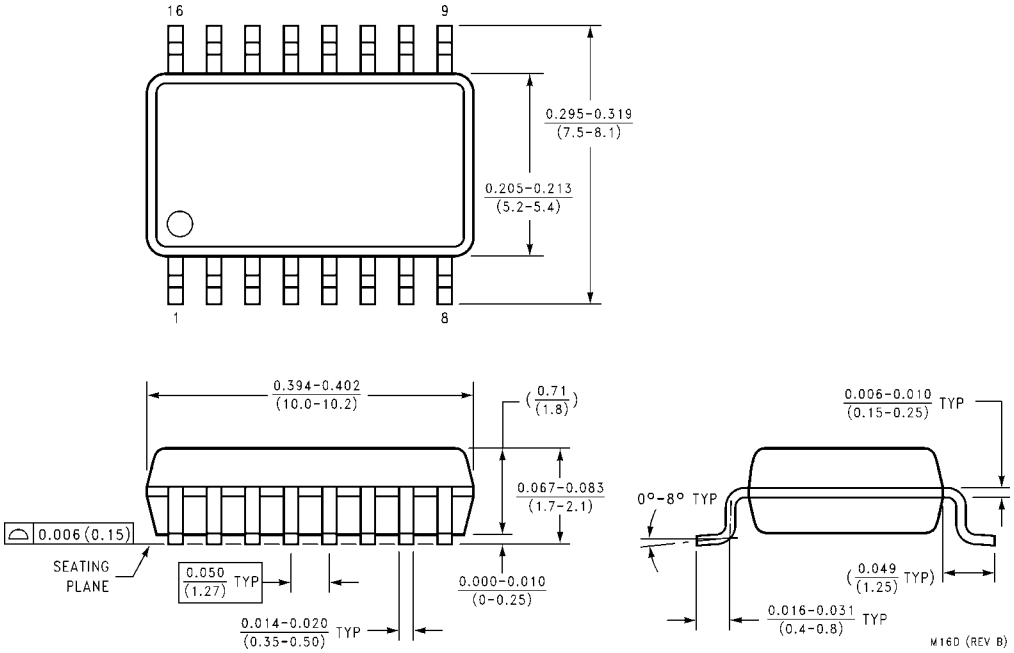
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0	7.0	10.0	4.0	12.0	4.0	11.0	ns
t_{PHL}	S to Z_n	3.0	5.0	7.0	3.0	9.0	3.0	8.0	
t_{PLH}	Propagation Delay	5.0	7.0	9.5	5.0	13.0	5.0	11.0	ns
t_{PHL}	$\overline{E}$ to Z_n	2.5	4.5	6.5	2.5	7.5	2.5	7.0	
t_{PLH}	Propagation Delay	2.5	4.5	6.0	2.5	7.5	2.5	6.5	ns
t_{PHL}	I_n to Z_n	2.5	4.0	5.5	1.5	7.5	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted

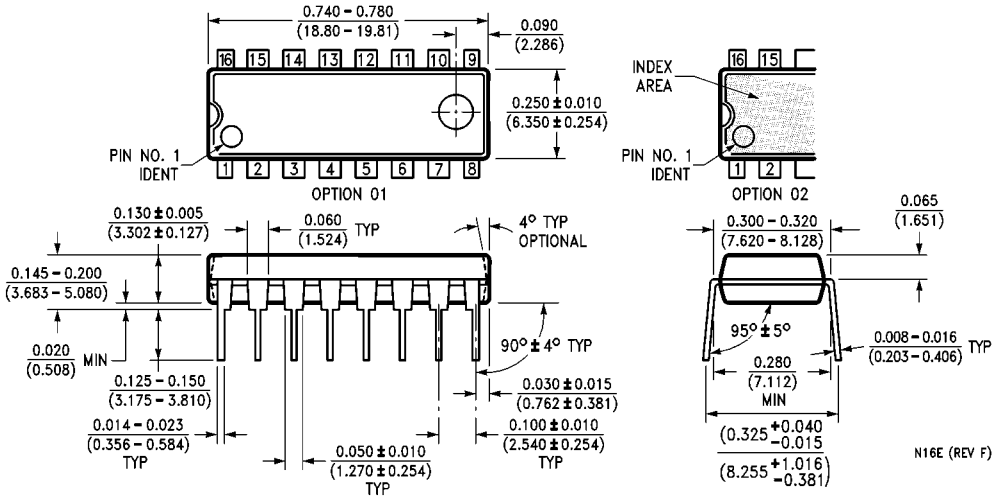


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F158A
Quad 2-Input Multiplexer

General Description

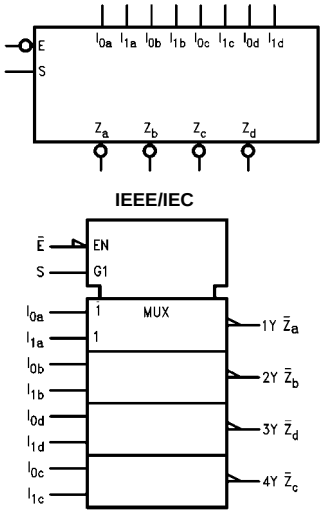
The F158A is a high speed quad 2-input multiplexer. It selects four bits of data from two sources using the common Select and Enable inputs. The four outputs present the selected data in the inverted form. The F158A can also generate any four of the 16 different functions of two variables.

Ordering Code:

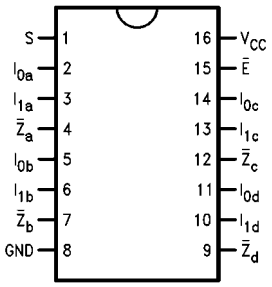
Order Number	Package Number	Package Description
74F158ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F158ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F158APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_{0a}–I_{0d}	Source 0 Data Inputs	1.0/1.0	20 μA/–0.6 mA
I_{1a}–I_{1d}	Source 1 Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{E}$	Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
S	Select Input	1.0/1.0	20 μA/–0.6 mA
$\overline{Z}_a$–$\overline{Z}_d$	Inverted Outputs	50/33.3	–1 mA/20 mA

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	$\overline{Z}$
H	X	X	X	H
L	L	L	X	H
L	L	H	X	L
L	H	X	L	H
L	H	X	H	L

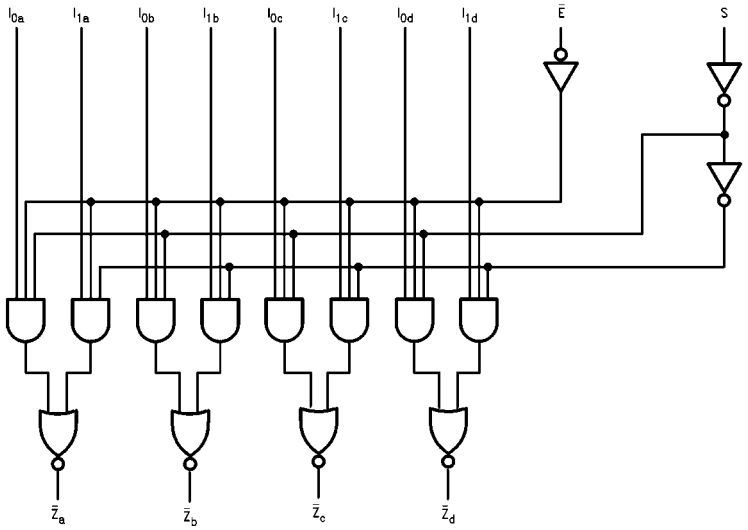
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
$\overline{Z}_n = \overline{E} \times (I_{1n}S + I_{0n}\overline{S})$

Functional Description

The F158A quad 2-input multiplexer selects four bits of data from two sources under the control of a common Select input (S) and presents the data in inverted form at the four outputs. The Enable input ($\overline{E}$) is active LOW. When $\overline{E}$ is HIGH, all of the outputs ($\overline{Z}$) are forced HIGH regardless of all other inputs. The F158A is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input.

A common use of the F158A is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The F158A can generate four functions of two variables with one variable common. This is useful for implementing gating functions.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

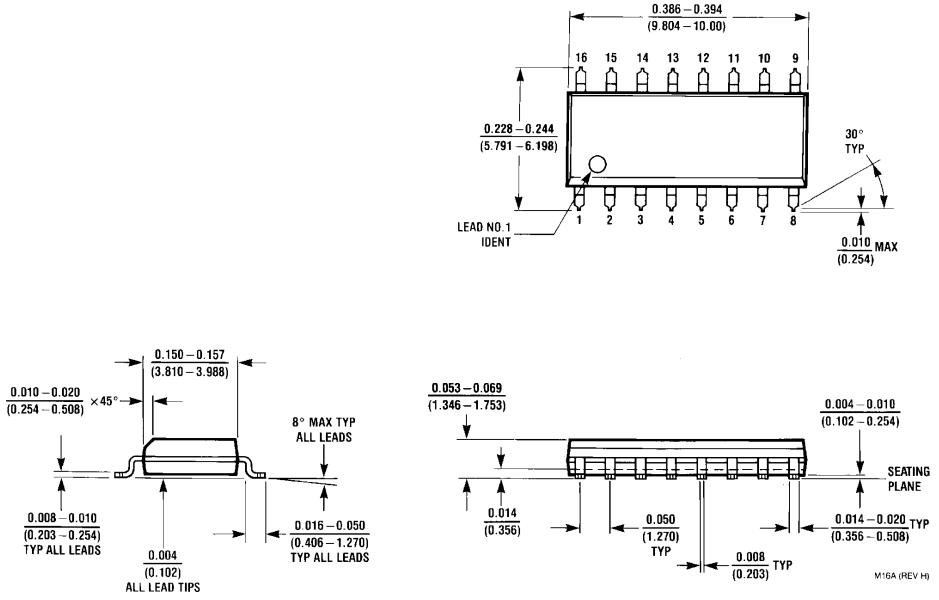
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			10	15	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			15	25	mA	Max	V_O = LOW

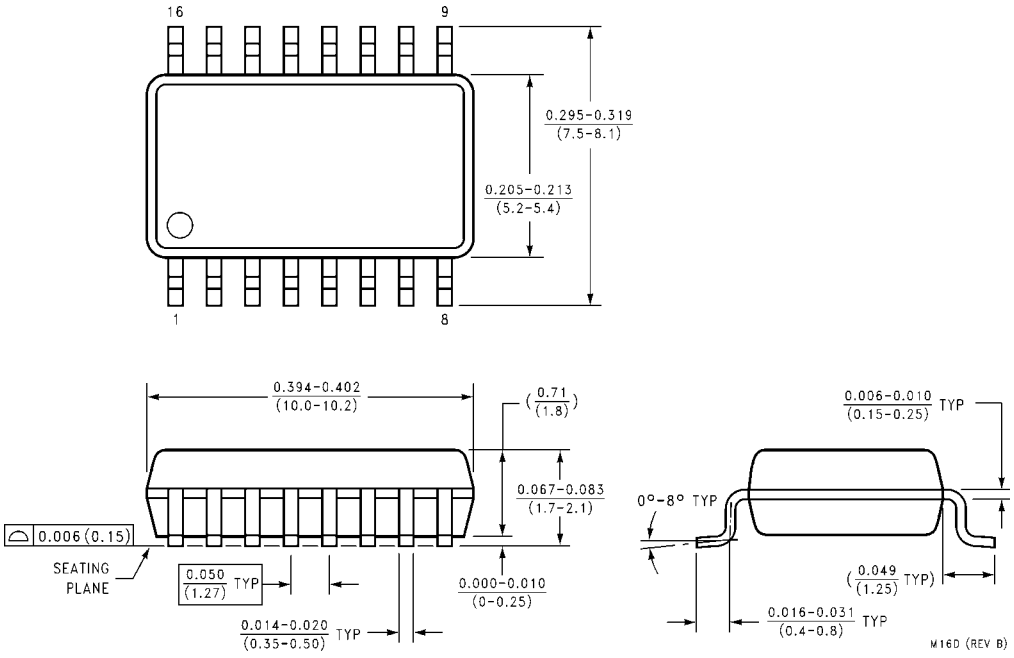
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	5.5	8.5	3.0	10.5	3.0	9.5	ns
t_{PHL}	S to $\overline{Z}_n$	2.5	4.5	6.5	2.5	8.0	2.5	7.0	
t_{PLH}	Propagation Delay	2.5	4.5	6.0	2.5	8.0	2.5	7.0	ns
t_{PHL}	$\overline{E}$ to $\overline{Z}_n$	2.0	4.0	6.0	2.0	7.0	2.0	6.5	
t_{PLH}	Propagation Delay	2.5	4.0	5.9	2.5	8.5	2.5	7.0	ns
t_{PHL}	I_n to $\overline{Z}_n$	1.5	2.5	4.0	1.0	5.0	1.5	4.5	

Physical Dimensions inches (millimeters) unless otherwise noted

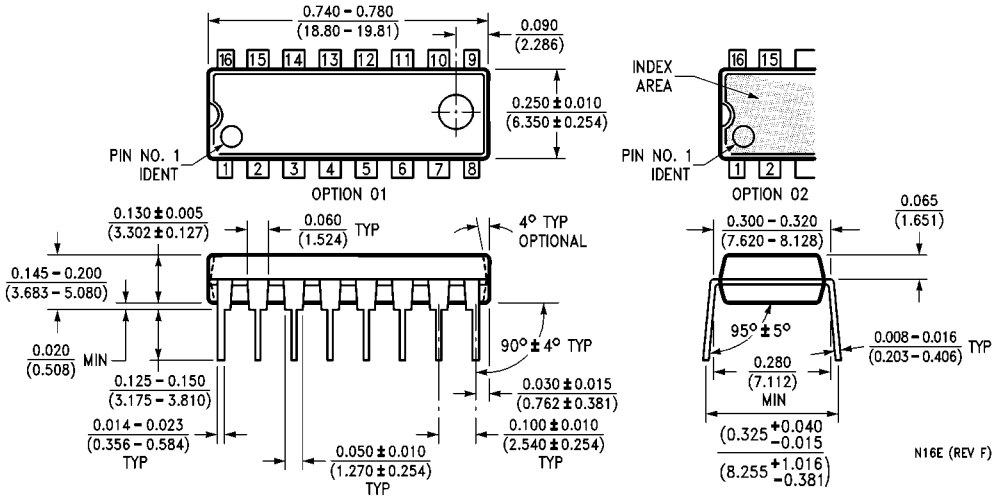


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F160A • 74F162A
Synchronous Presettable BCD Decade Counter

General Description

The 74F160A and 74F162A are high-speed synchronous decade counters operating in the BCD (8421) sequence. They are synchronously presettable for applications in programmable dividers. There are two types of Count Enable inputs plus a Terminal Count output for versatility in forming synchronous multistage counters. The F160A has an asynchronous Master Reset input that overrides all other inputs and forces the outputs LOW. The F162A has a Synchronous Reset input that overrides counting and parallel loading and allows all outputs to be simultaneously reset on the rising edge of the clock. The F160A and F162A are high speed versions of the F160 and F162.

Features

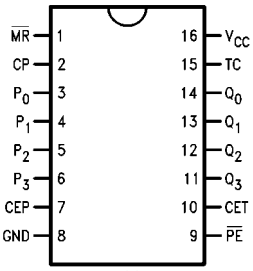
- Synchronous counting and loading
- High-speed synchronous expansion
- Typical count rate of 120 MHz

Ordering Code:

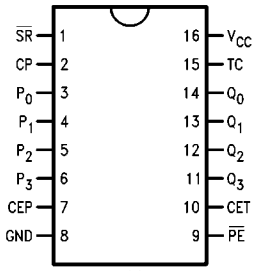
Order Number	Package Number	Package Description
74F160ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F160ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F160APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F162ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F162APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

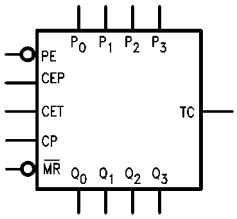


74F160A

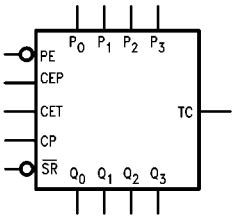


74F162A

Logic Symbols

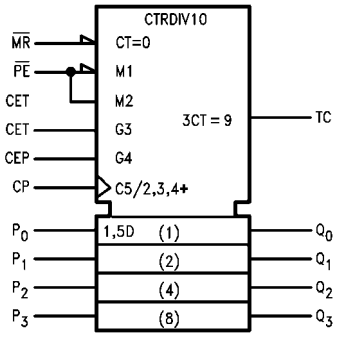


74F160A

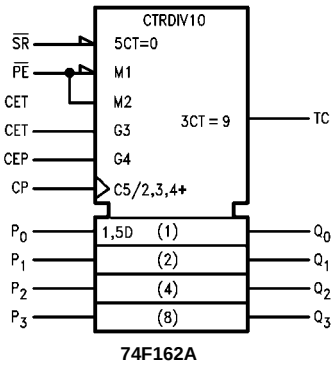


74F162A

IEEE/IEC



74F160A



74F162A

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
CEP	Count Enable Parallel Input	1.0/1.0	20 µA/–0.6 mA
CET	Count Enable Trickle Input	1.0/2.0	20 µA/–1.2 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{MR}$ (74F160A)	Asynchronous Master Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{SR}$ (74F162A)	Synchronous Reset Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{PE}$	Parallel Enable Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
TC	Terminal Count Output	50/33.3	–1 mA/20 mA

Functional Description

The 74F160A and 74F162A count modulo-10 in the BCD (8421) sequence. From state 9 (HLLH) they increment to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs (except due to Master Reset of the (F160A) occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: asynchronous reset (F160A), synchronous reset (F162A), parallel load, count-up and hold. Five control inputs—Master Reset ($\overline{MR}$, F160A), Synchronous Reset ($\overline{SR}$, F162A), Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides all other inputs and asynchronously forces all outputs LOW. A LOW signal on $\overline{SR}$ overrides counting and parallel loading and allows all outputs to go LOW on the next rising edge of CP. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{MR}$ (F160A) or $\overline{SR}$ (F162A) HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The F160A and F162A use D-type edge-triggered flip-flops and changing the $\overline{SR}$, $\overline{PE}$, CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 9. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways. Please refer to the F568 data sheet. The TC output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, counters or registers. In the F160A and F162A decade counters, the TC output is fully decoded and can only be HIGH in state 9. If a decade counter is preset to an illegal state, or assumes an illegal state when power is applied, it will return to the normal sequence within two counts, as shown in the State Diagram.

Logic Equations:

$$\text{Count Enable} = CEP \times CET \times \overline{PE}$$

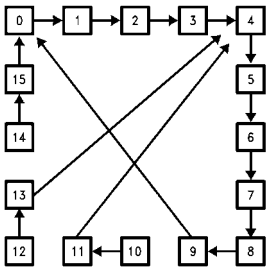
$$TC = Q_0 \times \overline{Q}_1 \times \overline{Q}_2 \times Q_3 \times CET$$

Mode Select Table

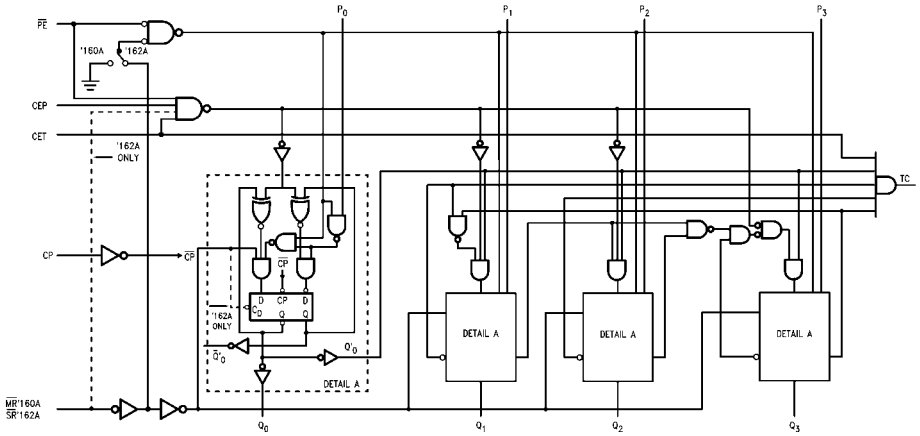
*$\overline{SR}$	$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (⌐)
L	X	X	X	Reset (Clear)
H	L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	H	Count (Increment)
H	H	L	X	No Change (Hold)
H	H	X	L	No Change (Hold)

*For 74'F162A only
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagram



Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (CP, CEP,P_n, $\overline{MR}$ (F160A))
				−1.2	mA	Max	V_{IN} = 0.5V (CET, $\overline{SR}$ (F162A), $\overline{PE}$)
I_{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current		37	55	mA	Max	V_O = HIGH

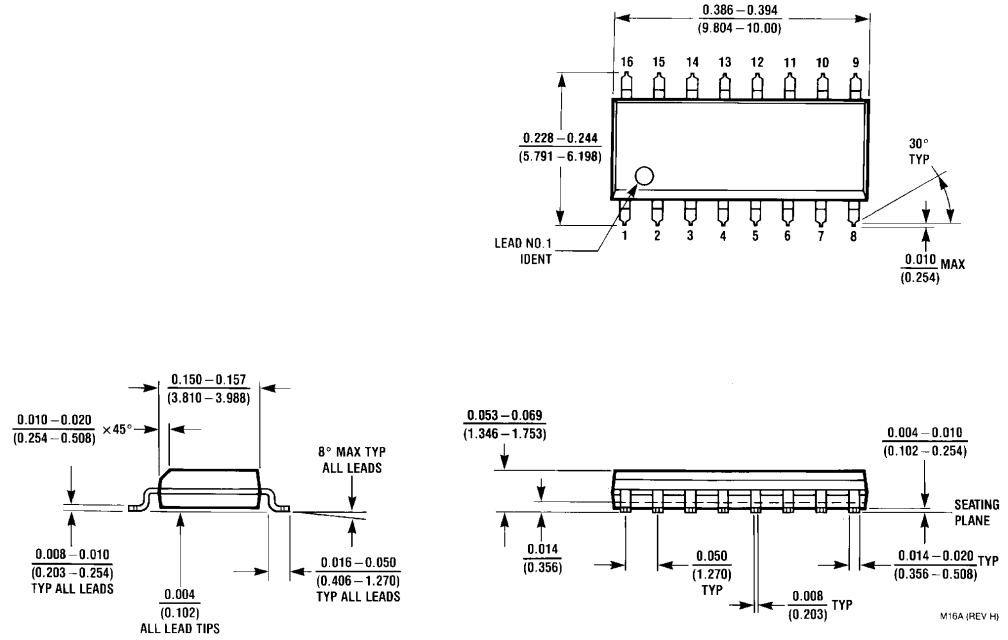
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	90	120		75		80		MHz
t_{PLH}	Propagation Delay, Count	3.5	5.5	7.5	3.5	9.0	3.5	8.5	ns
t_{PHL}	CP to Q_n ($\overline{PE}$ Input HIGH)	3.5	7.5	10.0	3.5	11.5	3.5	11.0	
t_{PLH}	Propagation Delay, Load	4.0	6.0	8.5	4.0	10.0	4.0	9.5	ns
t_{PHL}	CP to Q_n ($\overline{PE}$ Input LOW)	4.0	6.0	8.5	4.0	10.0	4.0	9.5	
t_{PLH}	Propagation Delay	5.0	10.0	14.0	5.0	16.5	5.0	15.0	ns
t_{PHL}	CP to TC	5.0	10.0	14.0	5.0	15.5	5.0	15.0	
t_{PLH}	Propagation Delay	2.5	4.5	7.5	2.5	9.0	2.5	8.5	ns
t_{PHL}	CET to TC	2.5	4.5	7.5	2.5	9.0	2.5	8.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n (74F160A)	5.5	9.0	12.0	5.5	14.0	5.5	13.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to TC (74F160A)	4.5	8.0	10.5	4.5	12.5	4.5	11.5	ns

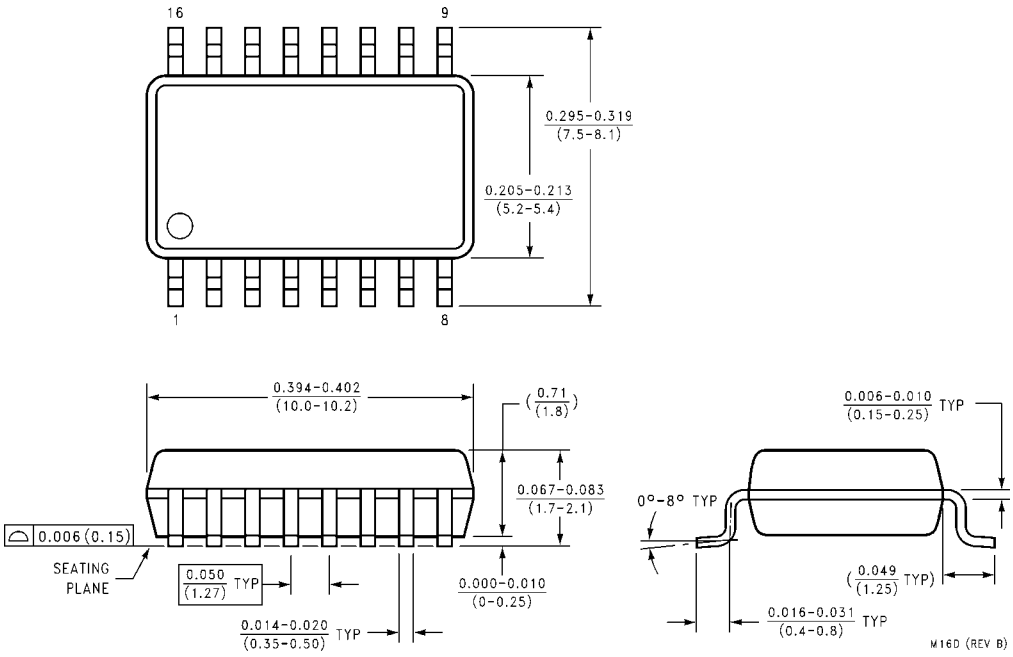
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		5.5		4.0		ns
$t_S(L)$	P_n to CP (74F160A)	5.0		5.5		5.0		
$t_S(H)$	Setup Time, HIGH or LOW	5.0				5.0		ns
$t_S(L)$	P_n to CP (74F162A)	5.0				5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.5		2.0		
$t_H(L)$	P_n to CP	2.0		2.5		2.0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		13.5		11.5		ns
$t_S(L)$	$\overline{PE}$ or $\overline{SR}$ to CP	8.5		10.5		9.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	$\overline{PE}$ or $\overline{SR}$ to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		13.0		11.5		ns
$t_S(L)$	CEP or CET to CP	5.0		6.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	CEP or CET to CP	0		0		0		
$t_W(H)$	Clock Pulse Width (Load)	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		
$t_W(H)$	Clock Pulse Width (Count)	4.0		5.0		4.0		ns
$t_W(L)$	HIGH or LOW	6.0		8.0		7.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW (74F160A)	5.0		5.0		5.0		
t_{REC}	Recovery Time $\overline{MR}$ to CP (74F160A)	6.0		6.0		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

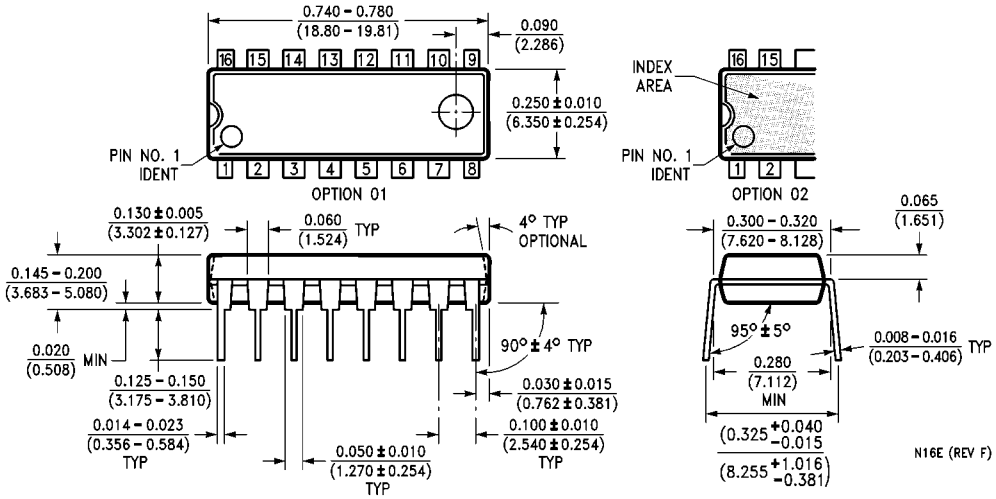


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F161A • 74F163A
Synchronous Presettable Binary Counter

General Description

The 74F161A and 74F163A are high-speed synchronous modulo-16 binary counters. They are synchronously presettable for application in programmable dividers and have two types of Count Enable inputs plus a Terminal Count output for versatility in forming synchronous multi-stage counters. The 74F161A has an asynchronous Master-Reset input that overrides all other inputs and forces the outputs LOW. The 74F163A has a Synchronous Reset input that overrides counting and parallel loading and allows the outputs to be simultaneously reset on the rising edge of the clock. The 74F161A and 74F163A are high-speed versions of the 74F161 and 74F163.

Features

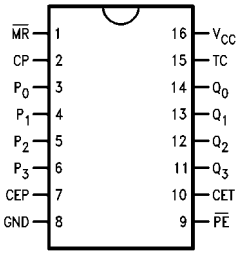
- Synchronous counting and loading
- High-speed synchronous expansion
- Typical count frequency of 120 MHz

Ordering Code:

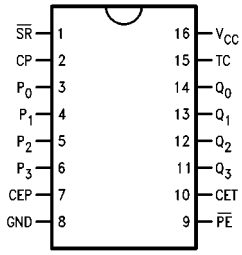
Order Number	Package Number	Package Description
74F161ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F161ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F161APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F163ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F163ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F163APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

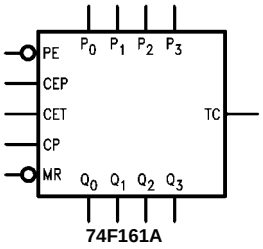


74F161A

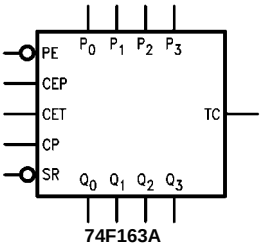


74F163A

Logic Symbols

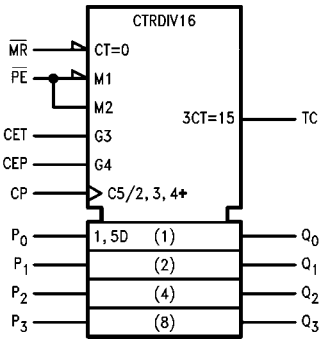


74F161A



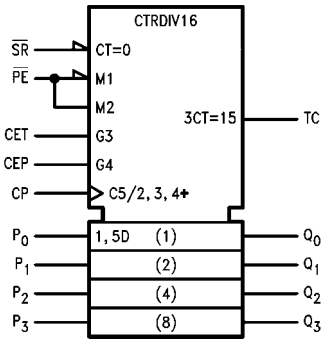
74F163A

IEEE/IEC



74F161A

IEEE/IEC



74F163A

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
CEP	Count Enable Parallel Input	1.0/1.0	20 µA/–0.6 mA
CET	Count Enable Trickle Input	1.0/2.0	20 µA/–1.2 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{MR}$ (74F161A)	Asynchronous Master Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{SR}$ (74F163A)	Synchronous Reset Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{PE}$	Parallel Enable Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
TC	Terminal Count Output	50/33.3	–1 mA/20 mA

Functional Description

The 74F161A and 74F163A count in modulo-16 binary sequence. From state 15 (HHHH) they increment to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs (except due to Master Reset of the 74F161A) occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: asynchronous reset (74F161A), synchronous reset (74F163A), parallel load, count-up and hold. Five control inputs—Master Reset ($\overline{MR}$, 74F161A), Synchronous Reset ($\overline{SR}$, 74F163A), Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides all other inputs and asynchronously forces all outputs LOW. A LOW signal on $\overline{SR}$ overrides counting and parallel loading and allows all outputs to go LOW on the next rising edge of CP. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{MR}$ ('F161A) or $\overline{SR}$ (74F163A) HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The 74F161A and 74F163A use D-type edge triggered flip-flops and changing the $\overline{SR}$, $\overline{PE}$, CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and the counter is in state 15. To implement synchronous multi-stage counters, the TC outputs can be used with the CEP and CET inputs in two different ways. Please refer to the 74F568 data sheet. The TC output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, counters or registers.

Logic Equations: Count Enable = CEP • CET • $\overline{PE}$

$$TC = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet CET$$

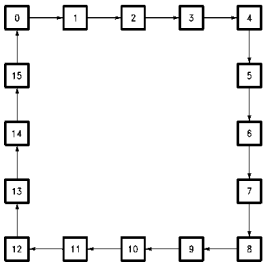
Mode Select Table

$\overline{SR}$ (Note 1)	$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (⌐)
L	X	X	X	Reset (Clear)
H	L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	H	Count (Increment)
H	H	L	X	No Change (Hold)
H	H	X	L	No Change (Hold)

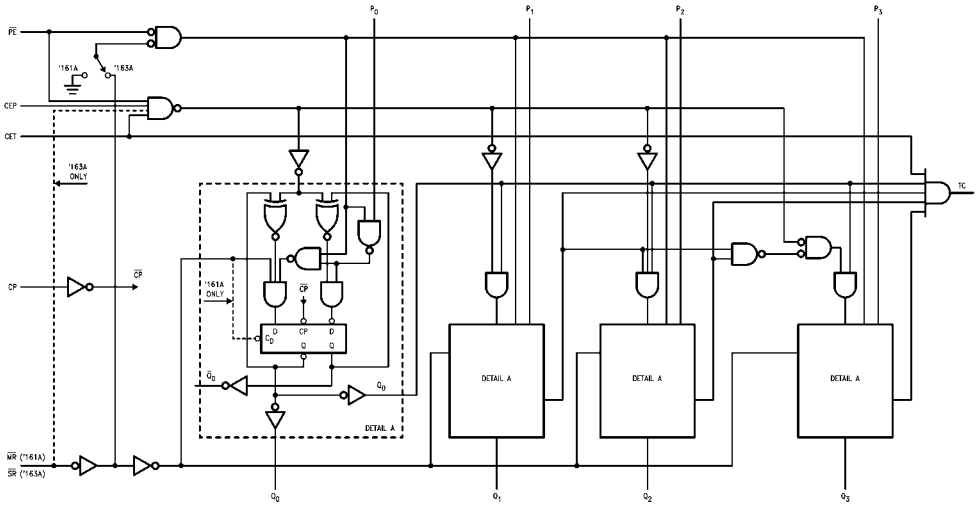
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Note 1: For 74F163A only

State Diagram



Block Diagram



Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	
		5% V_{CC}	2.7					
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (CEP, CP, $\overline{MR}$, P_0–P_3)
					−1.2	mA	Max	V_{IN} = 0.5V (CET, $\overline{PE}$, $\overline{SR}$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			37	55	mA	Max	

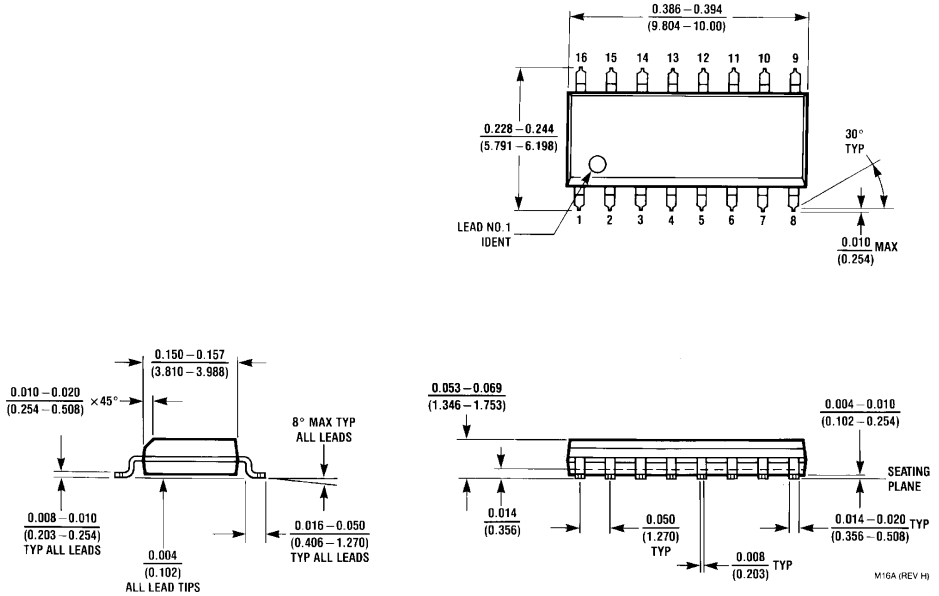
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50\ pF$			$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$ $C_L = 50\ pF$		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$ $C_L = 50\ pF$		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	100	120		75		90		MHz
t_{PLH}	Propagation Delay	3.5	5.5	7.5	3.5	9.0	3.5	8.5	ns
t_{PHL}	CP to Q_n ($\overline{PE}$ Input HIGH)	3.5	7.5	10.0	3.5	11.5	3.5	11.0	
t_{PLH}	Propagation Delay	4.0	6.0	8.5	4.0	10.0	4.0	9.5	ns
t_{PHL}	CP to Q_n ($\overline{PE}$ Input LOW)	4.0	6.0	8.5	4.0	10.0	4.0	9.5	
t_{PLH}	Propagation Delay	5.0	10.0	14.0	5.0	16.5	5.0	15.0	ns
t_{PHL}	CP to TC	5.0	10.0	14.0	5.0	15.5	5.0	15.0	
t_{PLH}	Propagation Delay	2.5	4.5	7.5	2.5	9.0	2.5	8.5	ns
t_{PHL}	CET to TC	2.5	4.5	7.5	2.5	9.0	2.5	8.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n (74F161A)	5.5	9.0	12.0	5.5	14.0	5.5	13.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to TC (74F161A)	4.5	8.0	10.5	4.5	12.5	4.5	11.5	ns

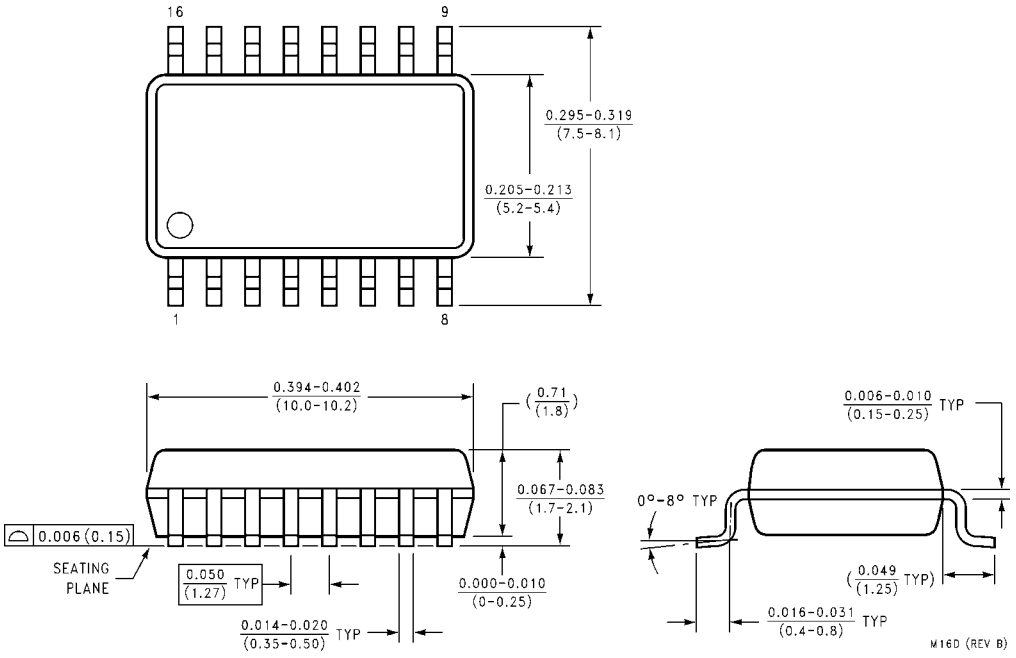
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	5.0		5.5		5.0		ns
$t_S(L)$	P_n to CP	5.0		5.5		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.5		2.0		ns
$t_H(L)$	P_n to CP	2.0		2.5		2.0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		13.5		11.5		ns
$t_S(L)$	$\overline{PE}$ or $\overline{SR}$ to CP	8.5		10.5		9.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		3.6		2.0		ns
$t_H(L)$	$\overline{PE}$ or $\overline{SR}$ to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		13.0		11.5		ns
$t_S(L)$	CEP or CET to CP	5.0		6.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		ns
$t_H(L)$	CEP or CET to CP	0		0		0		
$t_W(H)$	Clock Pulse Width (Load)	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		
$t_W(H)$	Clock Pulse Width (Count)	4.0		5.0		4.0		ns
$t_W(L)$	HIGH or LOW	6.0		8.0		7.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW (74F161A)	5.0		5.0		5.0		ns
t_{REC}	Recovery Time $\overline{MR}$ to CP (74F161A)	6.0		6.0		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

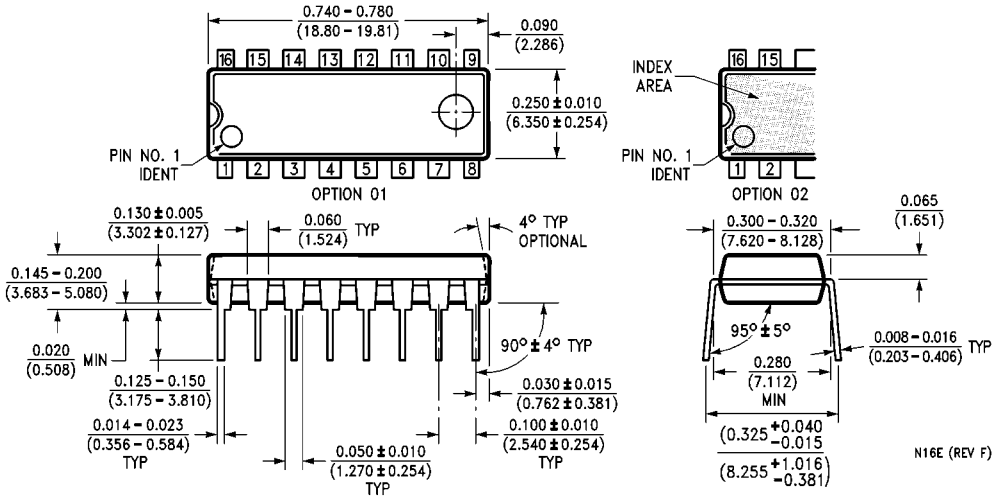


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

October 1989
Revised August 1999

74F164A
Serial-In, Parallel-Out Shift Register

General Description

The 74F164A is a high-speed 8-bit serial-in/parallel-out shift register. Serial data is entered through a 2-input AND gate synchronous with the LOW-to-HIGH transition of the clock. The device features an asynchronous Master Reset which clears the register, setting all outputs LOW independent of the clock. The 74F164A is a faster version of the 74F164.

Features

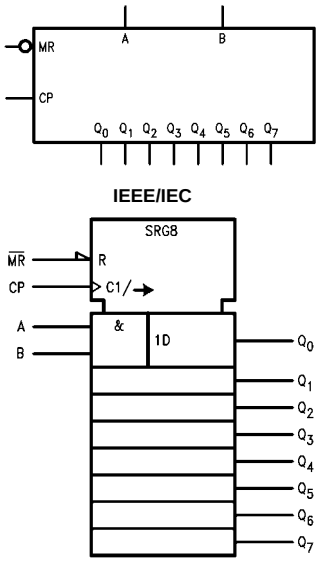
- Typical shift frequency of 90 MHz
- Asynchronous Master Reset
- Gated serial data input
- Fully synchronous data transfers
- 74F164A is a faster version of the 74F164

Ordering Code:

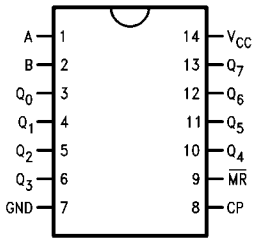
Order Number	Package Number	Package Description
74F164ASC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F164ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F164APC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A, B	Data Inputs	1.0/1.0	20 µA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{MR}$	Master Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
Q_0–Q_7	Outputs	50/33.3	–1 mA/20 mA

Functional Description

The 74F164A is an edge-triggered 8-bit shift register with serial data entry and an output from each of the eight stages. Data is entered serially through one of two inputs (A or B); either of these inputs can be used as an active HIGH Enable for data entry through the other input. An unused input must be tied HIGH.

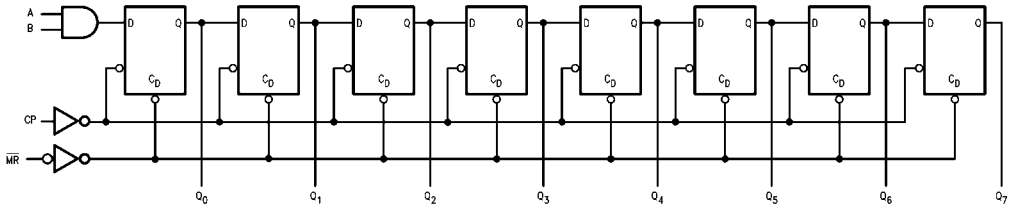
Each LOW-to-HIGH transition on the Clock (CP) input shifts data one place to the right and enters into Q_0 the logical AND of the two data inputs (A • B) that existed before the rising clock edge. A LOW level on the Master Reset ($\overline{MR}$) input overrides all other inputs and clears the register asynchronously, forcing all Q outputs LOW.

Mode Select Table

Operating Mode	Inputs			Outputs	
	$\overline{MR}$	A	B	Q_0	Q_1–Q_7
Reset (Clear)	L	X	X	L	L-L
Shift	H	l	l	L	q_0–q_6
	H	l	h	L	q_0–q_6
	H	h	l	L	q_0–q_6
	H	h	h	H	q_0–q_6

H(h) = HIGH Voltage Levels
L(l) = LOW Voltage Levels
X = Immaterial
q_n = Lower case letters indicate the state of the referenced input or output one setup time prior to the LOW-to-HIGH clock transition.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 1)	−0.5V to +7.0V
Input Current (Note 1)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			35	55	mA	Max	CP = HIGH $\overline{MR}$ = GND, A, B = GND

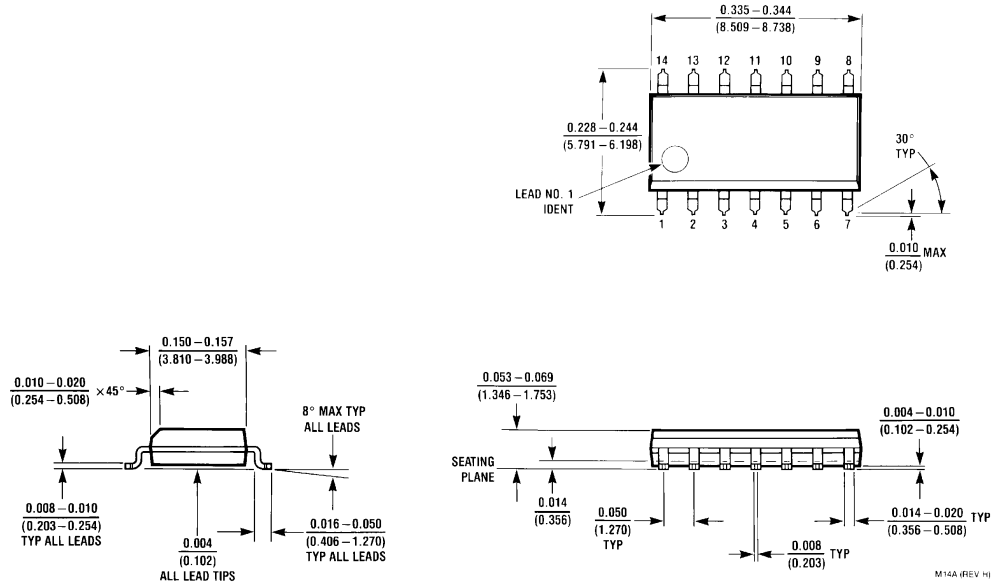
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	80	120		60		80		MHz
t_{PLH}	Propagation Delay	3.0	4.8	7.5	2.5	9.0	3.0	7.5	ns
t_{PHL}	CP to Q_n	3.5	5.0	8.0	3.0	8.5	3.5	8.0	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	7.0	10.0	4.0	12.5	5.0	10.5	ns

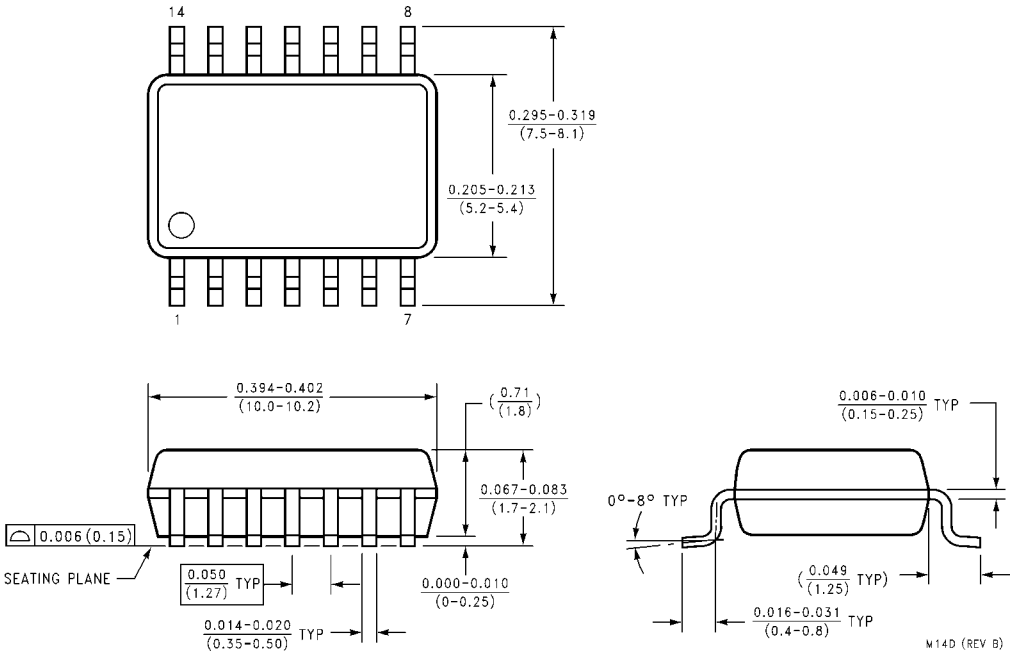
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.5		5.5		4.5		ns
$t_S(L)$	A or B to CP	4.0		4.0		4.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.0		1.0		
$t_H(L)$	A or B to CP	1.0		1.0		1.0		
$t_W(H)$	CP Pulse Width	4.0		4.0		4.0		ns
$t_W(L)$	HIGH or LOW	7.0		7.0		7.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	4.0		5.0		4.0		ns
t_{REC}	Recovery Time $\overline{MR}$ to CP	5.0		6.5		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

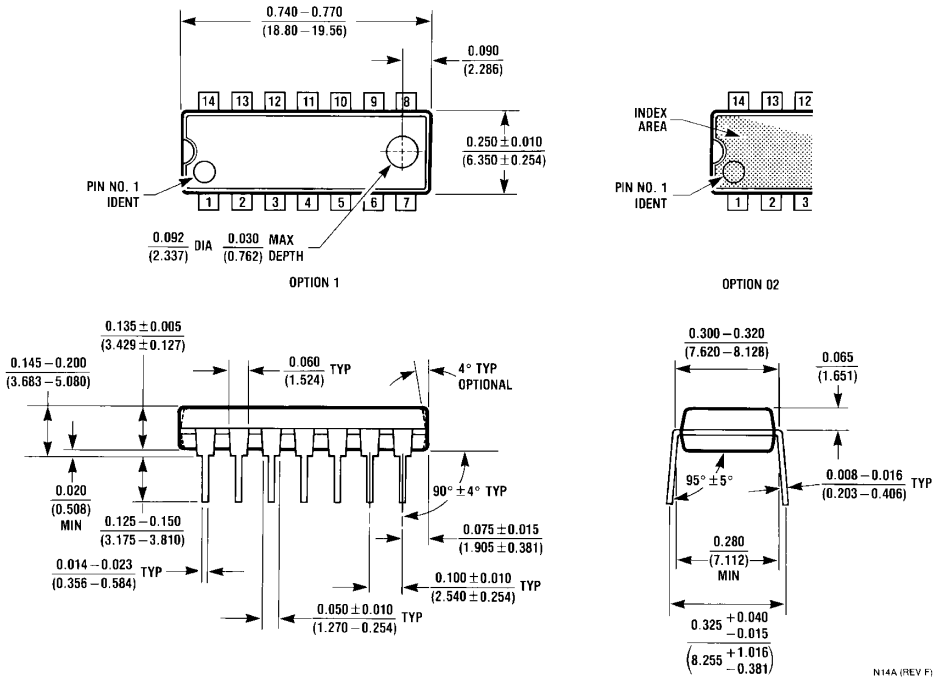


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F169
4-Stage Synchronous Bidirectional Counter

General Description

The 74F169 is a fully synchronous 4-stage up/down counter. The 74F169 is a modulo-16 binary counter. Features a preset capability for programmable operation, carry lookahead for easy cascading and a U/$\overline{D}$ input to control the direction of counting. All state changes, whether in counting or parallel loading, are initiated by the LOW-to-HIGH transition of the clock.

Features

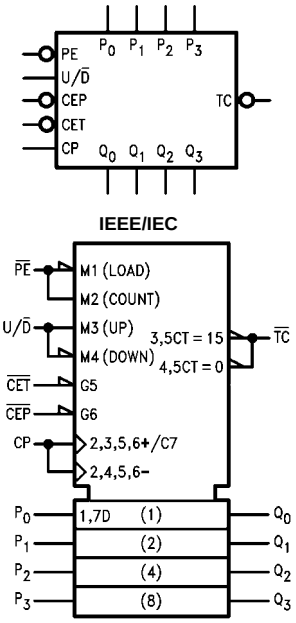
- Asynchronous counting and loading
- Built-in lookahead carry capability
- Presettable for programmable operation

Ordering Code:

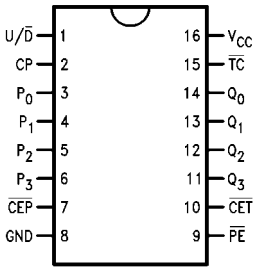
Order Number	Package Number	Package Description
74F169SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F169SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F169PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{CEP}$	Count Enable Parallel Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{CET}$	Count Enable Trickle Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{PE}$	Parallel Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
U/$\overline{D}$	Up-Down Count Control Input	1.0/1.0	20 µA/–0.6 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
$\overline{TC}$	Terminal Count Output (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The 74F169 uses edge-triggered J-K type flip-flops and has no constraints on changing the control or data input signals in either state of the clock. The only requirement is that the various inputs attain the desired state at least a setup time before the rising edge of the clock and remain valid for the recommended hold time thereafter. The parallel load operation takes precedence over other operations, as indicated in the Mode Select Table. When $\overline{PE}$ is LOW, the data on the P_0–P_3 inputs enters the flip-flops on the next rising edge of the clock. In order for counting to occur, both $\overline{CEP}$ and $\overline{CET}$ must be LOW and $\overline{PE}$ must be HIGH; the U/$\overline{D}$ input then determines the direction of counting. The Terminal Count ($\overline{TC}$) output is normally HIGH and goes LOW, provided that $\overline{CET}$ is LOW, when a counter reaches zero in the Count Down mode or reaches 15 for the 74F169 in the Count Up mode. The $\overline{TC}$ output state is not a function of the Count Enable Parallel ($\overline{CEP}$) input level. Since the $\overline{TC}$ signal is derived by decoding the flip-flop states, there exists the possibility of decoding spikes on $\overline{TC}$. For this reason the use of $\overline{TC}$ as a clock signal is not recommended (see logic equations below).

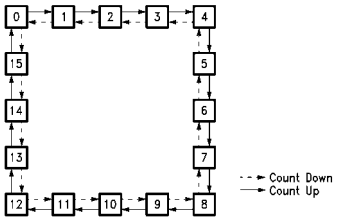
1. Count Enable = $\overline{CEP} \bullet \overline{CET} \bullet \overline{PE}$
2. Up: (74F169): $\overline{TC} = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet$ (Up) $\bullet \overline{CET}$
3. Down: $\overline{TC} = \overline{Q}_0 \bullet \overline{Q}_1 \bullet \overline{Q}_2 \bullet \overline{Q}_3 \bullet$ (Down) $\bullet \overline{CET}$

Mode Select Table

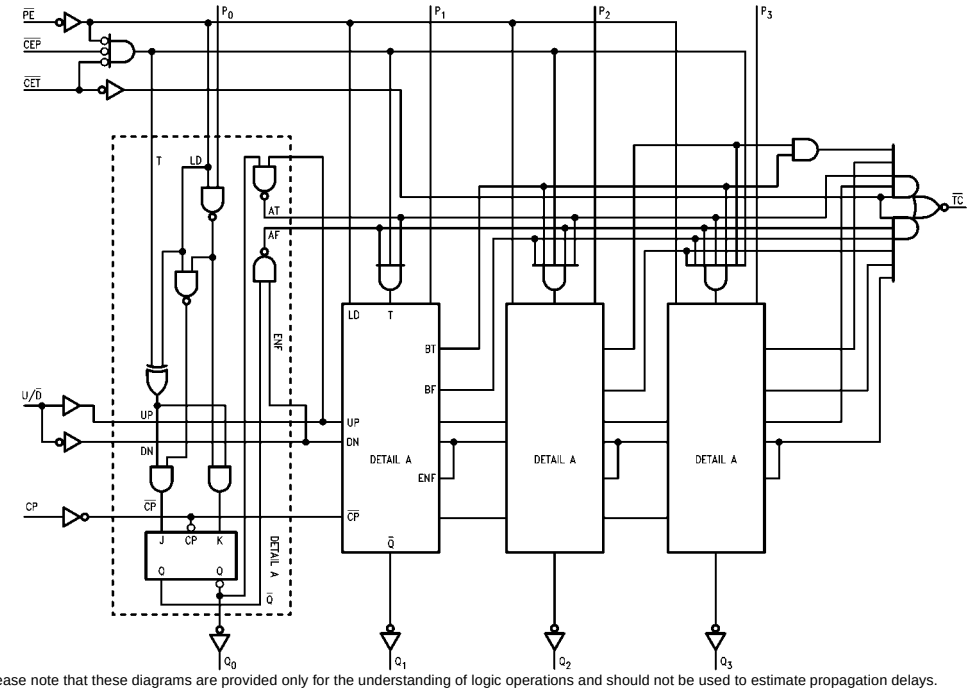
$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	U/$\overline{D}$	Action on Rising Clock Edge
L	X	X	X	Load ($P_n \rightarrow Q_n$)
H	L	L	H	Count Up (Increment)
H	L	L	L	Count Down (Decrement)
H	H	X	X	No Change (Hold)
H	X	H	X	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagram



Logic Diagram



Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (except $\overline{CET}$)
				−1.2			V_{IN} = 0.5V ($\overline{CET}$)
I_{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V_{OUT} = 0V
I_{CCL}	Power Supply Current		35	52	mA	Max	V_O = LOW

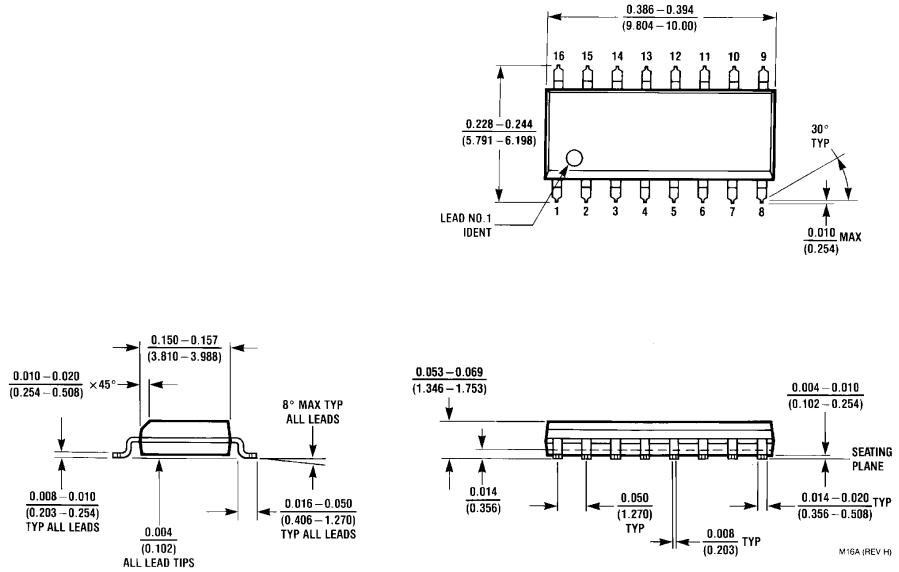
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	90			60		70		MHz
t_{PLH}	Propagation Delay	3.0	6.5	8.5	3.0	12.0	3.0	9.5	ns
t_{PHL}	CP to Q_n ($\overline{PE}$ HIGH or LOW)	4.0	9.0	11.5	4.0	16.0	4.0	13.0	
t_{PLH}	Propagation Delay	5.5	12.0	15.5	5.5	20.0	5.5	17.5	ns
t_{PHL}	CP to $\overline{TC}$	4.0	8.5	12.5	4.0	15.0	4.0	13.0	
t_{PLH}	Propagation Delay	2.5	4.5	6.5	2.5	9.0	2.5	7.0	ns
t_{PHL}	$\overline{CET}$ to $\overline{TC}$	2.5	8.5	11.0	2.5	12.0	2.5	12.0	
t_{PLH}	Propagation Delay	3.5	8.5	11.5	3.5	16.0	3.5	12.5	ns
t_{PHL}	U/$\overline{D}$ to $\overline{TC}$	4.0	8.0	12.0	4.0	14.0	4.0	13.0	

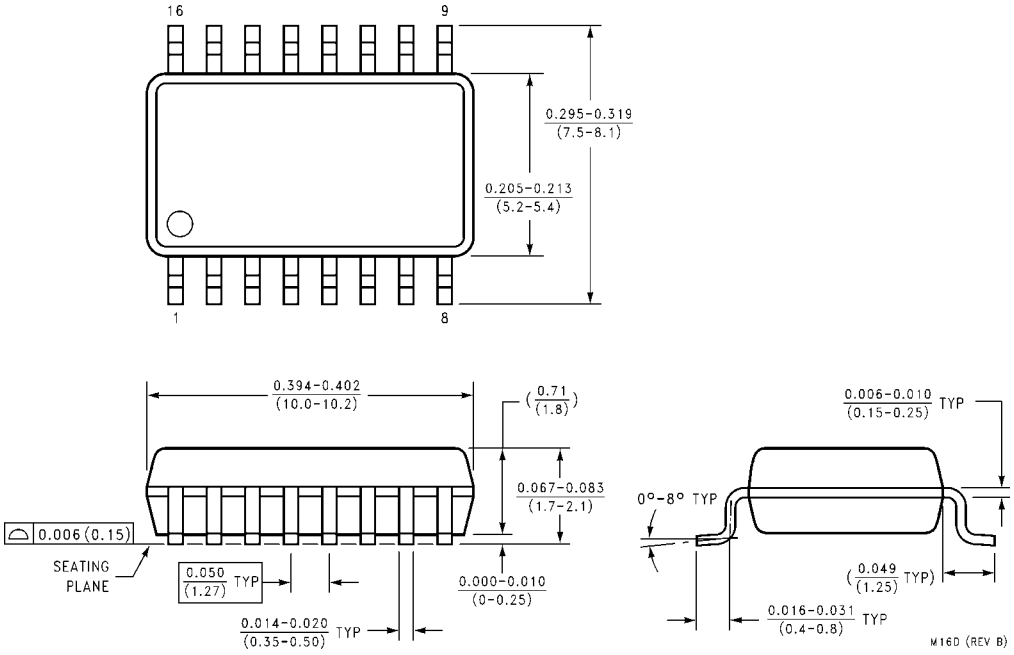
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		4.5		4.5		ns
$t_S(L)$	P_n to CP	4.0		4.5		4.5		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.5		3.5		
$t_H(L)$	P_n to CP	3.0		3.5		3.5		
$t_S(H)$	Setup Time, HIGH or LOW	7.0		8.0		8.0		ns
$t_S(L)$	$\overline{CEP}$ or $\overline{CET}$ to CP	5.0		8.0		6.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	$\overline{CEP}$ or $\overline{CET}$ to CP	0.5		1.0		0.5		
$t_S(H)$	Setup Time, HIGH or LOW	8.0		10.0		9.0		ns
$t_S(L)$	$\overline{PE}$ to CP	8.0		10.0		9.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.0		1.0		
$t_H(L)$	$\overline{PE}$ to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		14.0		12.5		ns
$t_S(L)$	U/$\overline{D}$ to CP	7.0		12.0		8.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	U/$\overline{D}$ to CP	0		0		0		
$t_W(H)$	CP Pulse Width	4.0		6.0		4.5		ns
$t_W(L)$	HIGH or LOW	7.0		9.0		8.0		

Physical Dimensions inches (millimeters) unless otherwise noted

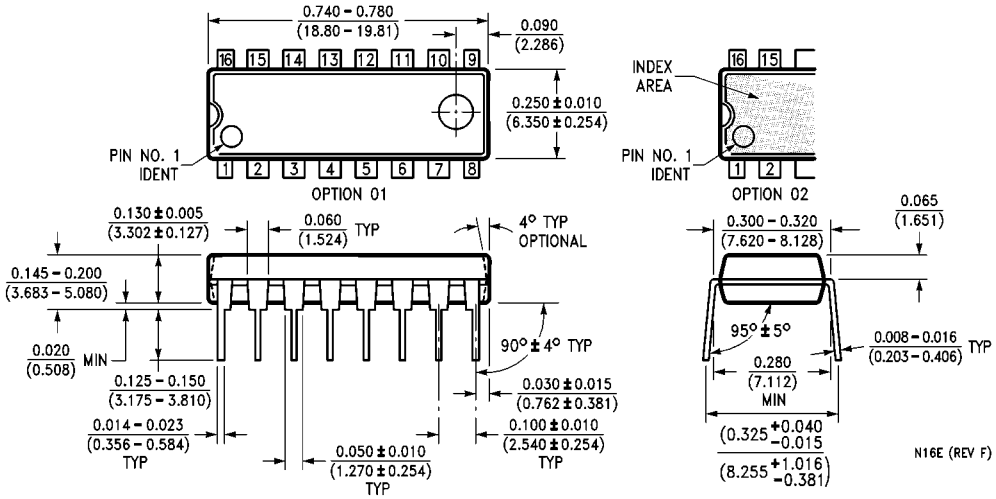


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F174
Hex D-Type Flip-Flop with Master Reset

General Description

The 74F174 is a high-speed hex D-type flip-flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the LOW-to-HIGH clock transition. The device has a Master Reset to simultaneously clear all flip-flops.

Features

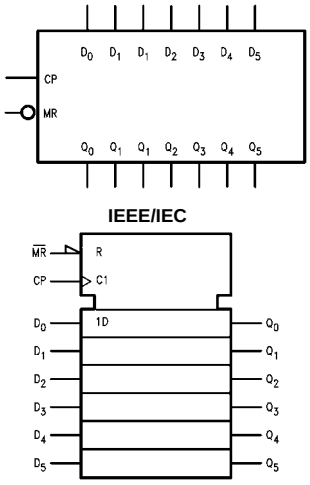
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Asynchronous common reset
- Guaranteed 4000V minimum ESD protection

Ordering Code:

Order Number	Package Number	Package Description
74F174SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F174SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F174PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

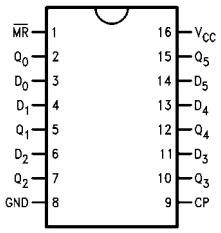
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_5	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{MR}$	Master Reset Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_5	Outputs	50/33.3	–1 mA/20 mA

Functional Description

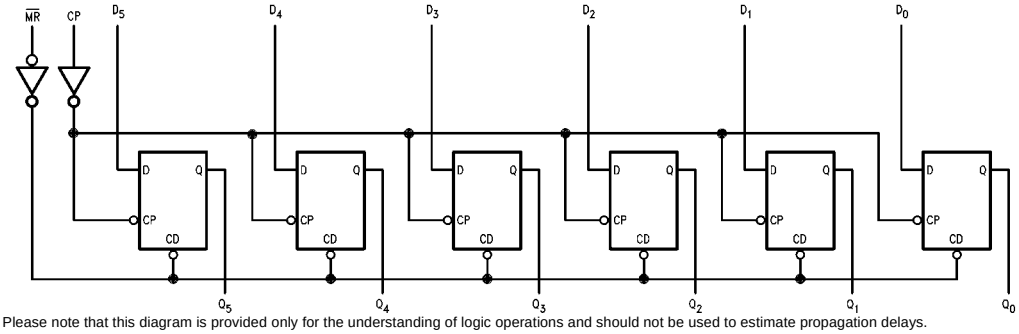
The 74F174 consists of six edge-triggered D-type flip-flops with individual D inputs and Q outputs. The Clock (CP) and Master Reset ($\overline{MR}$) are common to all flip-flops. Each D input's state is transferred to the corresponding flip-flop's output following the LOW-to-HIGH Clock (CP) transition. A LOW input to the Master Reset ($\overline{MR}$) will force all outputs LOW independent of Clock or Data inputs. The 74F174 is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Truth Table

Inputs			Outputs
$\overline{MR}$	CP	D_n	Q_n
L	X	X	L
H	⌐	H	H
H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
	Voltage	10% V_{CC}			0.5			I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			30	45	mA	Max	CP = ⌐‾ D_n = $\overline{MR}$ = HIGH
I_{CCL}	Power Supply Current			30	45	mA	Max	V_O = LOW

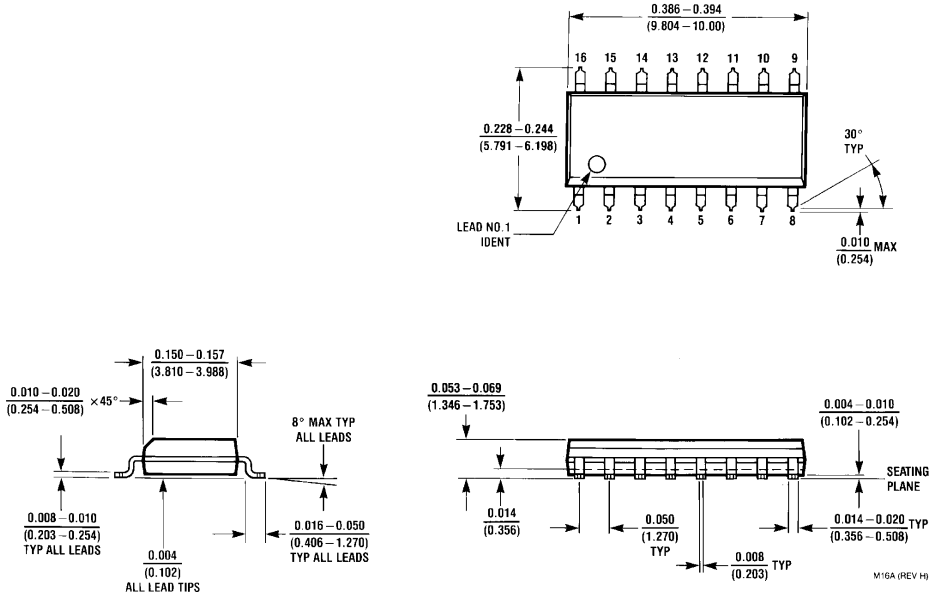
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	80			70		80		MHz
t_{PLH}	Propagation Delay	3.5	5.5	8.0	3.0	10.0	3.5	9.0	ns
t_{PHL}	CP to Q_n	4.0	7.0	10.0	4.0	12.0	4.0	11.0	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	5.0	10.0	14.0	5.0	16.0	5.0	15.0	ns

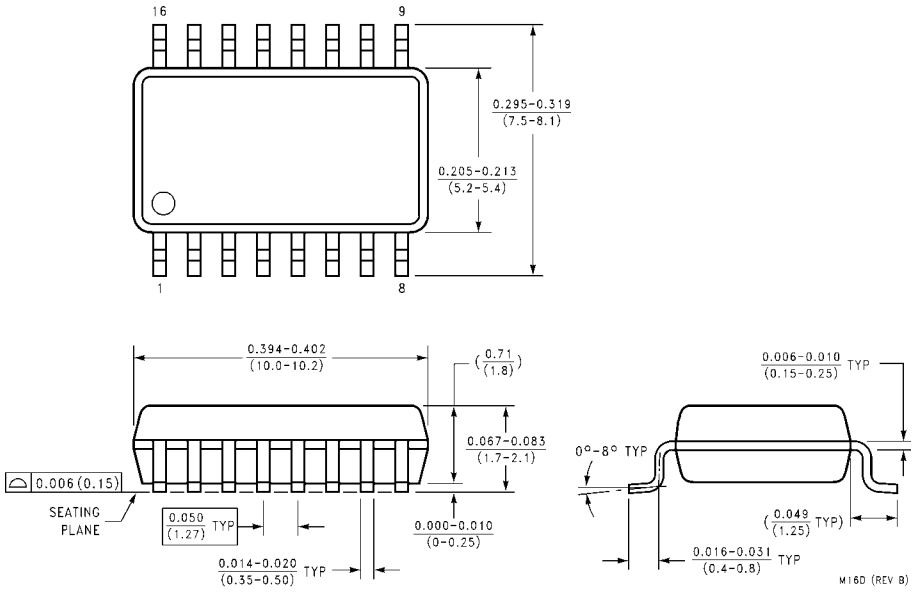
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.8		5.0		4.8		ns
$t_S(L)$	D_n to CP	4.0		5.0		4.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		2.0		0		
$t_H(L)$	D_n to CP	0		2.0		0		
$t_W(H)$	CP Pulse Width	4.0		5.0		4.0		ns
$t_W(L)$	HIGH or LOW	6.0		7.5		6.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	5.0		6.5		5.0		ns
t_{REC}	Recovery Time, $\overline{MR}$ to CP	5.0		6.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted

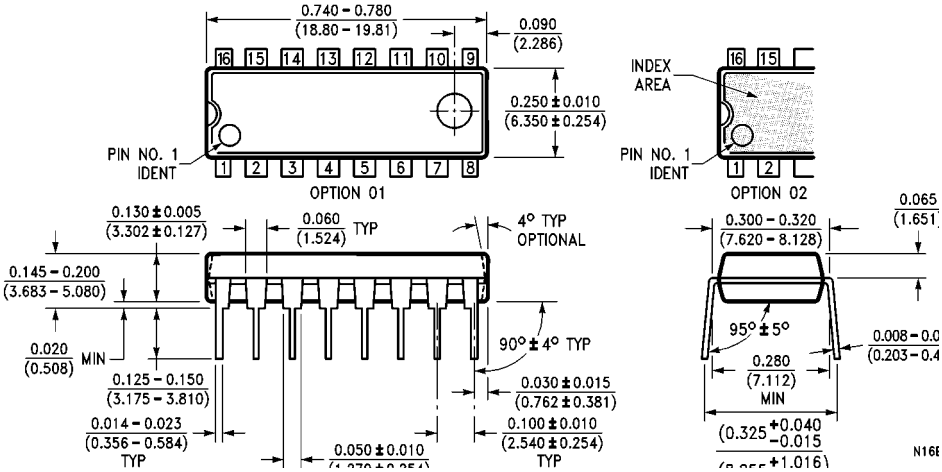


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F175
Quad D-Type Flip-Flop

General Description

The 74F175 is a high-speed quad D-type flip-flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D inputs is stored during the LOW-to-HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D inputs, LOW.

Features

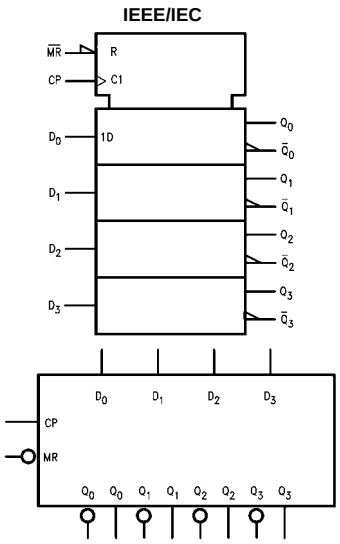
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Asynchronous common reset
- True and complement output

Ordering Code:

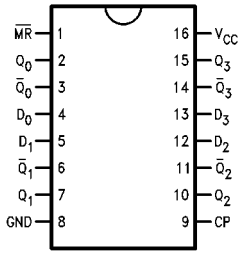
Order Number	Package Number	Package Description
74F175SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F175SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F175PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_3	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{MR}$	Master Reset Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_3	True Outputs	50/33.3	–1 mA/20 mA
$\overline{Q}_0$–$\overline{Q}_3$	Complement Outputs	50/33.3	–1 mA/20 mA

Functional Description

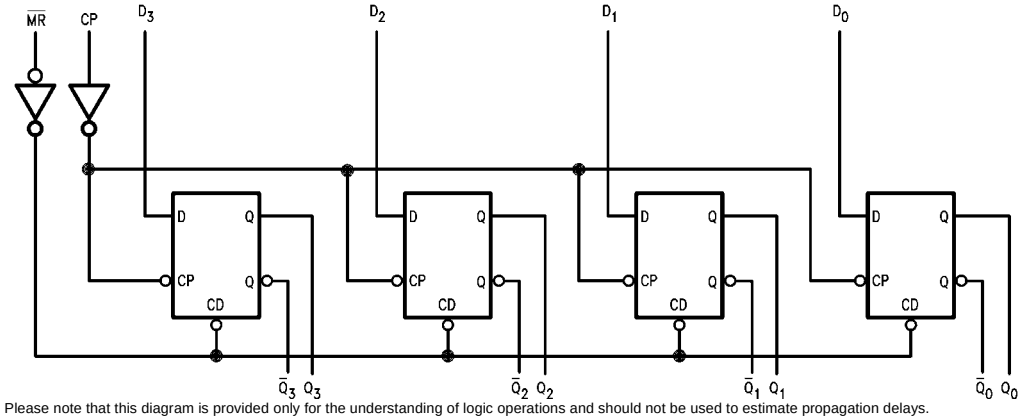
The 74F175 consists of four edge-triggered D-type flip-flops with individual D inputs and Q and $\overline{Q}$ outputs. The Clock and Master Reset are common. The four flip-flops will store the state of their individual D inputs on the LOW-to-HIGH clock (CP) transition, causing individual Q and $\overline{Q}$ outputs to follow. A LOW input on the Master Reset ($\overline{MR}$) will force all Q outputs LOW and $\overline{Q}$ outputs HIGH independent of Clock or Data inputs. The 74F175 is useful for general logic applications where a common Master Reset and Clock are acceptable.

Truth Table

Inputs			Outputs	
$\overline{MR}$	CP	D_n	Q_n	$\overline{Q}_n$
L	X	X	L	H
H	⌐	H	H	L
H	⌐	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			22.5	34.0	mA	Max	CP = ⌐ D_n = $\overline{MR}$ = HIGH

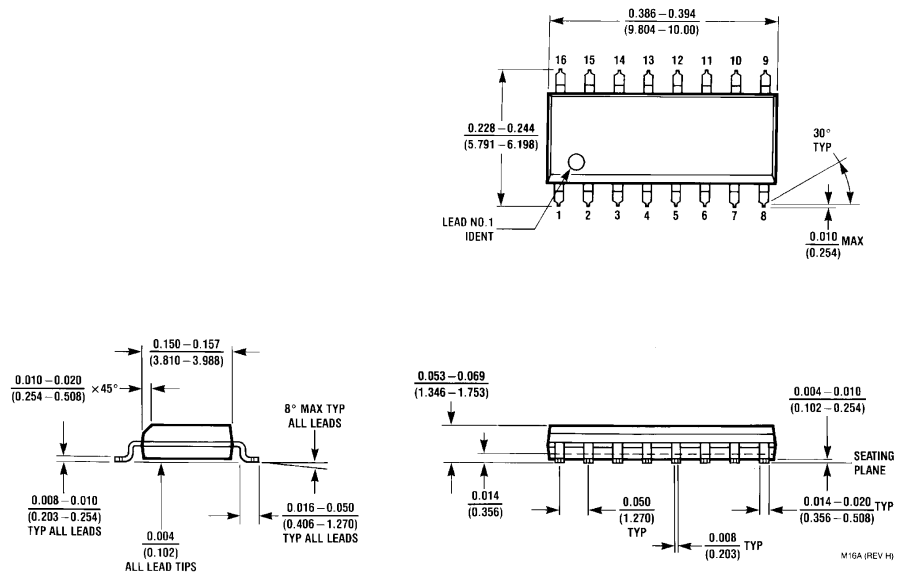
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	140		80		100		MHz
t_{PLH}	Propagation Delay	4.0	5.0	6.5	3.5	8.5	4.0	7.5	ns
t_{PHL}	CP to Q_n or $\overline{Q}_n$	4.0	6.5	8.5	4.0	10.5	4.0	9.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	4.5	9.0	11.5	4.5	15.0	4.5	13.0	ns
t_{PLH}	Propagation Delay $\overline{MR}$ to $\overline{Q}_n$	4.0	6.5	8.0	4.0	10.0	4.0	9.0	ns

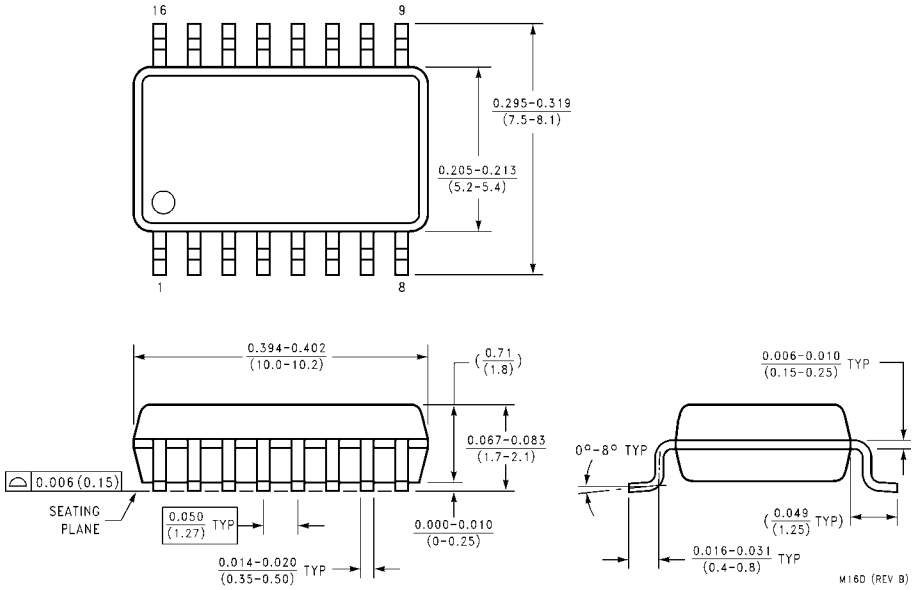
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.0		3.0		ns
$t_S(L)$	D_n to CP	3.0		3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.0		1.0		
$t_H(L)$	D_n to CP	1.0		2.0		1.0		
$t_W(H)$	CP Pulse Width	4.0		4.0		4.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	5.0		5.0		5.0		ns
t_{REC}	Recovery Time, $\overline{MR}$ to CP	5.0		5.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

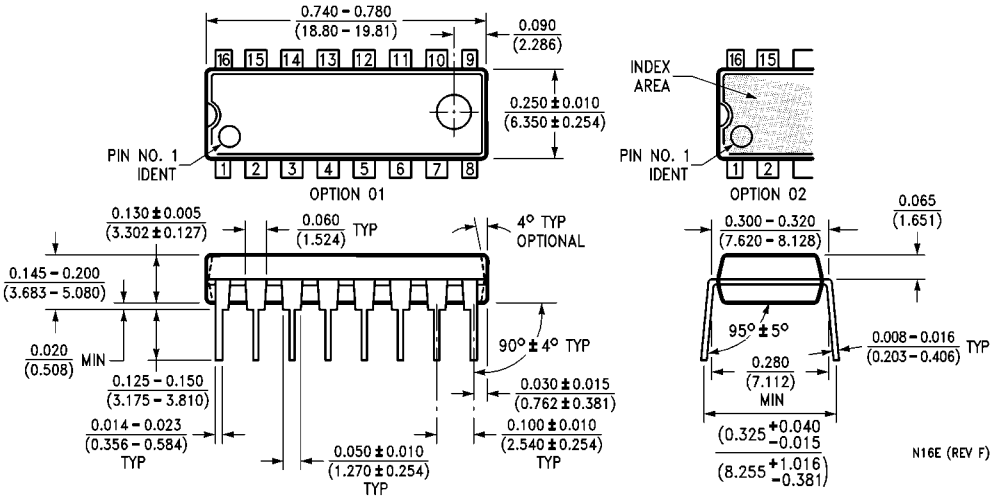


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F181
4-Bit Arithmetic Logic Unit

General Description

The 74F181 is a 4-bit Arithmetic logic Unit (ALU) which can perform all the possible 16 logic operations on two variables and a variety of arithmetic operations. It is 40% faster than the Schottky ALU and only consumes 30% as much power.

Features

- Full lookahead for high-speed arithmetic operation on long words

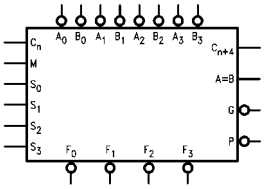
Ordering Code:

Order Number	Package Number	Package Description
74F181SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F181PC	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
74F181SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

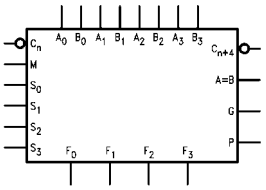
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols

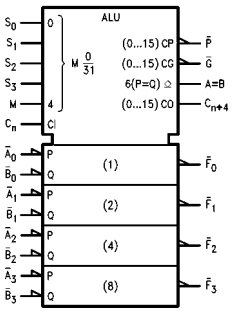
Active-HIGH Operands



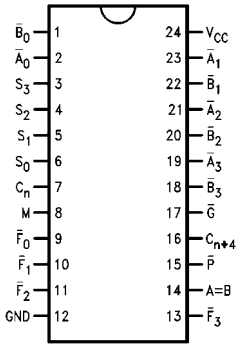
Active-LOW Operands



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{A}_0$–$\overline{A}_3$	A Operand Inputs (Active LOW)	1.0/3.0	20 μA/–1.8 mA
$\overline{B}_0$–$\overline{B}_3$	B Operand Inputs (Active LOW)	1.0/3.0	20 μA/–1.8 mA
S_0–S_3	Function Select Inputs	1.0/4.0	20 μA/–2.4 mA
M	Mode Control Input	1.0/1.0	20 μA/–0.6 mA
C_n	Carry Input	1.0/5.0	20 μA/–3.0 mA
$\overline{F}_0$–$\overline{F}_3$	Function Outputs (Active LOW)	50/33.3	–1 mA/20 mA
A = B	Comparator Output	OC (Note 1)/33.3	(Note 1)/20 mA
$\overline{G}$	Carry Generate Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{P}$	Carry Propagate Output (Active LOW)	50/33.3	–1 mA/20 mA
C_{n+4}	Carry Output	50/33.3	–1 mA/20 mA

Note 1: OC-Open Collector

Functional Description

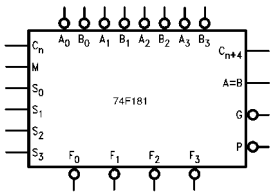
The 74F181 is a 4-bit high-speed parallel Arithmetic Logic Unit (ALU). Controlled by the four Function Select inputs (S_0–S_3) and the Mode Control input (M), it can perform all the 16 possible logic operations or 16 different arithmetic operations on Active HIGH or Active LOW operands. The Function Table lists these operations.

When the Mode Control input (M) is HIGH, all internal carries are inhibited and the device performs logic operations on the individual bits as listed. When the Mode Control input is LOW, the carries are enabled and the device performs arithmetic operations on the two 4-bit words. The device incorporates full internal carry lookahead and provides for either ripple carry between devices using the C_{n+4} output, or for carry lookahead between packages using the signals $\overline{P}$ (Carry Propagate) and $\overline{G}$ (Carry Generate). In the Add mode, $\overline{P}$ indicates that $\overline{F}$ is 15 or more, while $\overline{G}$ indicates that $\overline{F}$ is 16 or more. In the Subtract mode $\overline{P}$ indicates that $\overline{F}$ is zero or less, while $\overline{G}$ indicates that $\overline{F}$ is less than zero. $\overline{P}$ and $\overline{G}$ are not affected by carry in. When speed requirements are not stringent, the 74F181 can be used in a simple Ripple Carry mode by connecting the Carry output (C_n+4) signal to the Carry input (C_n) of the next unit. For high speed operation the device is used in conjunction with a carry lookahead circuit. One carry lookahead package is required for each group of four 74F181 devices. Carry lookahead can be provided at various levels and offers high speed capability over extremely long word lengths.

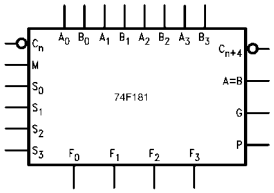
The A = B output from the device goes HIGH when all four $\overline{F}$ outputs are HIGH and can be used to indicate logic equivalence over four bits when the unit is in the Subtract mode. The A = B output is open collector and can be wired AND with other A = B outputs to give a comparison for more than four bits. The A = B signal can also be used with the C_{n+4} signal to indicate A > B and A < B.

The Function Table lists the arithmetic operations that are performed without a carry in. An incoming carry adds a one to each operation. Thus, select code LHHL generates A minus B minus 1 (2s complement notation) without a carry in and generates A minus B when a carry is applied. Because subtraction is actually performed by complementary addition (1s complement), a carry out means borrow; thus a carry is generated when there is no underflow and no carry is generated when there is underflow. As indicated, this device can be used with either active LOW inputs producing active LOW outputs or with active HIGH inputs producing active HIGH outputs. For either case the table lists the operations that are performed to the operands labeled inside the logic symbol.

Operation Table

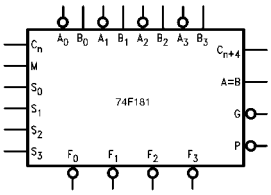
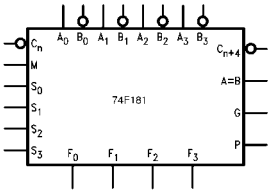


a. All Input Data Inverted

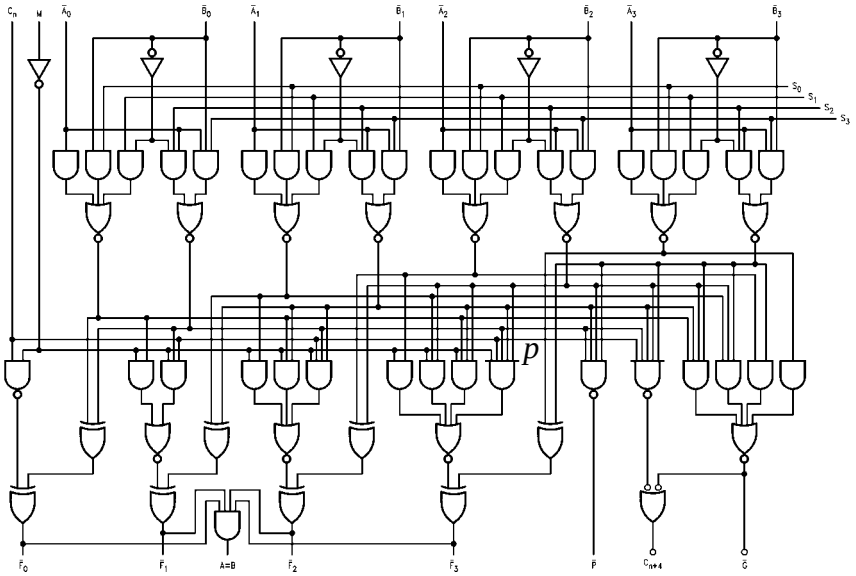


b. All Input Data True

S_0	S_1	S_2	S_3	Logic (M=H)	Arithmetic (M=L, C_0=Inactive)	Arithmetic (M=L, C_0=Active)
L	L	L	L	$\overline{A}$	A minus 1	A
H	L	L	L	$\overline{A} \cdot \overline{B}$	A • B minus 1	A • B
L	H	L	L	$\overline{A} + B$	A • $\overline{B}$ minus 1	A • $\overline{B}$
H	H	L	L	Logic “1”	minus 1 (2s comp.)	Zero
L	L	H	L	$\overline{A} + \overline{B}$	A plus (A + $\overline{B}$)	A plus (A + $\overline{B}$) plus 1
H	L	H	L	$\overline{B}$	A • B plus (A + $\overline{B}$)	A • B plus (A + $\overline{B}$) plus 1
L	H	H	L	$\overline{A \oplus B}$	A minus B minus 1	A minus B
H	H	H	L	A + $\overline{B}$	A + $\overline{B}$	A + $\overline{B}$ plus 1
L	L	L	H	$\overline{A} \cdot B$	A plus (A + B)	A plus (A + B plus 1
H	L	L	H	A⊕B	A plus B	A plus B plus 1
L	H	L	H	B	A • $\overline{B}$ plus (A + B)	A • $\overline{B}$ plus (A + B) plus 1
H	H	L	H	A + B	A + B	A + B plus 1
L	L	H	H	Logic “0”	A plus A (2 × A)	A plus A (2 × A) plus 1
H	L	H	H	A • $\overline{B}$	A plus A • B	A plus A • B plus 1
L	H	H	H	A • B	A plus A • $\overline{B}$	A plus A • $\overline{B}$ plus 1
H	H	H	H	A	A	A plus 1
L	L	L	L	$\overline{A}$	A	A plus 1
H	L	L	L	$\overline{A} + \overline{B}$	A + B	A + B plus 1
L	H	L	L	$\overline{A} \cdot B$	A + $\overline{B}$	A + $\overline{B}$ plus 1
H	H	L	L	Logic “0”	minus 1 (2s comp.)	Zero
L	L	H	L	$\overline{A} \cdot \overline{B}$	A plus (A • $\overline{B}$)	A plus A • $\overline{B}$ plus 1
H	L	H	L	$\overline{B}$	A • $\overline{B}$ plus (A + B)	A • B plus (A + B) plus 1
L	H	H	L	A ⊕ B	A minus B minus 1	A minus B
H	H	H	L	A • $\overline{B}$	A • $\overline{B}$ minus 1	A • $\overline{B}$
L	L	L	H	$\overline{A} + B$	A plus A • B	A plus A • B plus 1
H	L	L	H	$\overline{A \oplus B}$	A plus B	A plus B plus 1
L	H	L	H	B	A • B plus (A + $\overline{B}$)	A • B plus (A + $\overline{B}$) plus 1
H	H	L	H	A • B	A • B minus 1	A • B
L	L	H	H	Logic “1”	A plus A (2 × A)	A plus A (2 × A) plus 1
H	L	H	H	A + $\overline{B}$	A plus (A + B)	A plus (A+B) plus 1
L	H	H	H	A + B	A plus (A + $\overline{B}$)	A plus (A+$\overline{B}$) plus 1
H	H	H	H	A	A minus 1	A

	S_0	S_1	S_2	S_3	Logic (M=H)	Arithmetic (M=L, C_0=Inactive)	Arithmetic (M=L, C_0=Active)
 **c. A All Input Data Inverted; B Input Data True**	L	L	L	L	$\overline{A}$	A minus 1	A
	H	L	L	L	$\overline{A} + B$	$A \cdot \overline{B}$ minus 1	$A \cdot B$
	L	H	L	L	$\overline{A} \cdot \overline{B}$	$A \cdot B$ minus 1	$A \cdot B$
	H	H	L	L	Logic “1”	minus 1 (2s comp.)	Zero
	L	L	H	L	$\overline{A} \cdot B$	A plus $(A + B)$	A plus $(A + B)$ plus 1
	H	L	H	L	B	$A \cdot \overline{B}$ plus $(A + B)$	$A \cdot \overline{B}$ plus $(A + B)$ plus 1
	L	H	H	L	$A \oplus B$	A plus B	A plus B plus 1
	H	H	H	L	$A + B$	$A + B$	$A + B$ plus 1
	L	L	L	H	$\overline{A + B}$	A plus $(A + \overline{B})$	A plus $(A + \overline{B})$ plus 1
	H	L	L	H	$\overline{A \oplus B}$	A minus B minus 1	A minus B
	L	H	L	H	$\overline{B}$	$A \cdot B$ plus $(A + \overline{B})$	$A \cdot B$ plus $(A + \overline{B})$ plus 1
	H	H	L	H	$A + \overline{B}$	$A + \overline{B}$	$A + \overline{B}$ plus 1
	L	L	H	H	Logic “0”	A plus A $(2 \times A)$	A plus A $(2 \times A)$ plus 1
	H	L	H	H	$A \cdot B$	A plus $A \cdot \overline{B}$	A plus $A \cdot \overline{B}$ plus 1
	L	H	H	H	$A \cdot \overline{B}$	A plus $A \cdot B$	A plus $A \cdot B$ plus 1
	H	H	H	H	A	A	A plus 1
 **d. A Input Data True; B Input Date Inverted**	L	L	L	L	$\overline{A}$	A	A plus 1
	H	L	L	L	$\overline{A} \cdot B$	$A + \overline{B}$	$A + \overline{B}$ plus 1
	L	H	L	L	$\overline{A + B}$	$A + B$	$A + B$ plus 1
	H	H	L	L	Logic “0”	minus 1 (2s comp.)	Zero
	L	L	H	L	$\overline{A} + B$	A plus $A \cdot B$	A plus $A \cdot B$ plus 1
	H	L	H	L	B	$A \cdot B$ plus $(A + \overline{B})$	$A \cdot \overline{B}$ plus $(A + B)$ plus 1
	L	H	H	L	$\overline{A \oplus B}$	A plus B	A plus B plus 1
	H	H	H	L	$A \cdot B$	$A \cdot B$ minus 1	$A \cdot B$
	L	L	L	H	$\overline{A} \cdot \overline{B}$	A plus $A \cdot \overline{B}$	A plus $A \cdot B$ plus 1
	H	L	L	H	$A \oplus B$	A minus B minus 1	A minus B
	L	H	L	H	$\overline{B}$	$A \cdot \overline{B}$ plus $(A + B)$	$A \cdot \overline{B}$ plus $(A + B)$ plus 1
	H	H	L	H	$A \cdot \overline{B}$	$A \cdot \overline{B}$ minus 1	$A \cdot \overline{B}$
	L	L	H	H	Logic “1”	A plus A $(2 \times A)$	A plus A $(2 \times A)$ plus 1
	H	L	H	H	$A + B$	A plus $(A + \overline{B})$	A plus $(A + \overline{B})$ plus 1
	L	H	H	H	$A + \overline{B}$	A plus $(A + B)$	A plus $(A + B)$ plus 1
	H	H	H	H	A	A minus 1	A

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

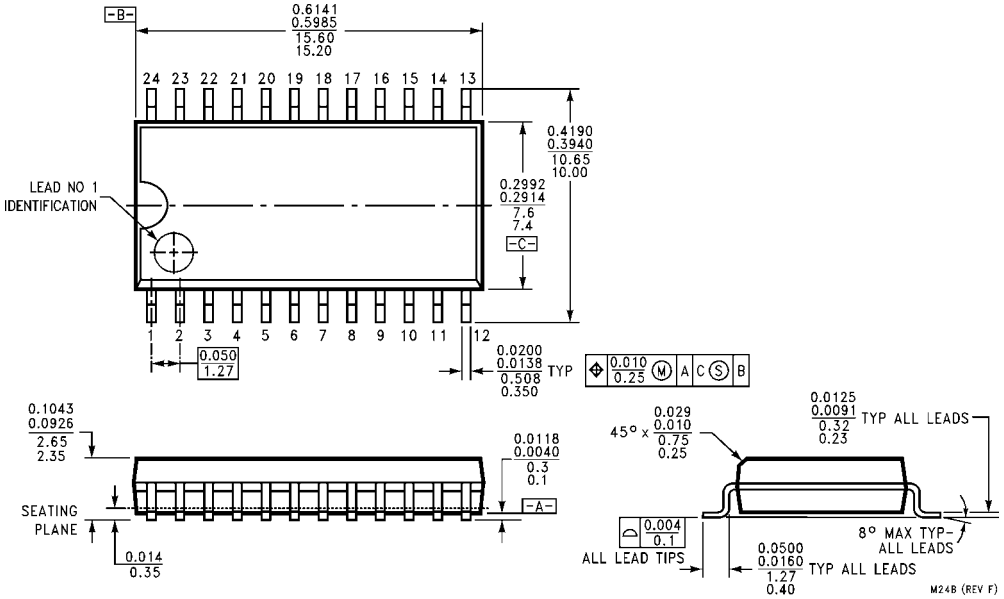
DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} ($\overline{F}_n$, $\overline{G}$, $\overline{P}$, C_{n+4})
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (M)
				−1.8			V_{IN} = 0.5V ($\overline{A}_0$, $\overline{A}_1$, $\overline{A}_3$, $\overline{B}_0$, $\overline{B}_1$, $\overline{B}_3$)
				−2.4			V_{IN} = 0.5V (S_n, $\overline{A}_2$, $\overline{B}_2$)
				−3.0			V_{IN} = 0.5V (C_n)
I_{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V_{OUT} = 0V ($\overline{F}_n$, $\overline{G}$, $\overline{P}$, C_{n+4})
I_{OHC}	Open Collector, Output OFF Leakage Test			250	µA	Min	V_O = V_{CC} (A = B)
I_{CCH}	Power Supply Current		43	65.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		43	65.0	mA	Max	V_O = LOW

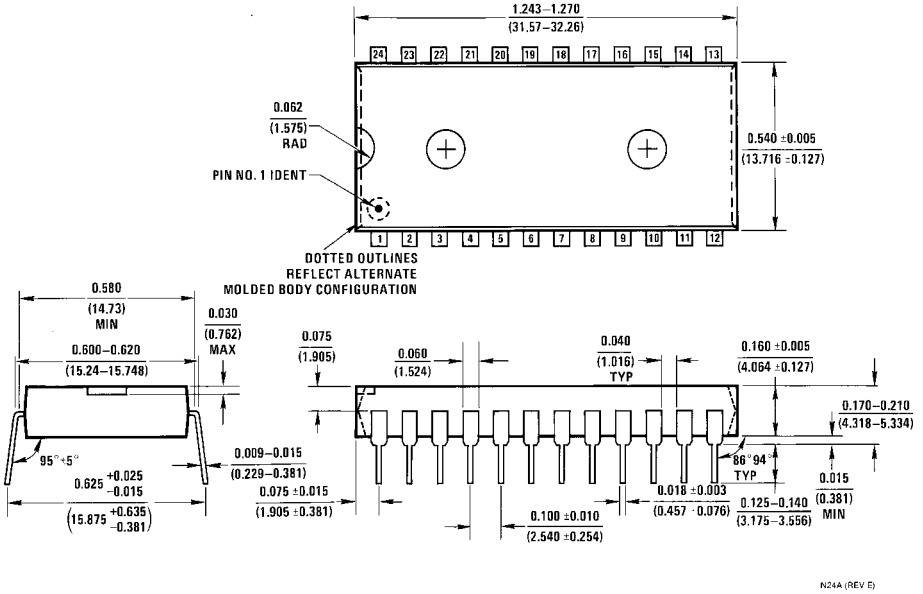
AC Electrical Characteristics

Symbol	Parameter		$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
	Path	Mode	Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay		3.0	6.4	8.5	3.0	10.0	3.0	9.5	ns
t_{PHL}	C_n to C_{n+4}		3.0	6.1	8.0	3.0	9.5	3.0	9.0	
t_{PLH}	Propagation Delay		5.0	10.0	13.0	5.0	15.5	5.0	14.0	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to C_{n+4}	Sum	4.0	9.4	12.0	3.5	16.5	4.0	13.0	
t_{PLH}	Propagation Delay		5.0	10.8	14.0	5.0	17.0	5.0	15.0	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to C_{n+4}	Dif	5.0	10.0	13.0	4.0	15.0	5.0	14.0	
t_{PLH}	Propagation Delay		3.0	6.7	8.5	2.5	16.0	3.0	9.5	ns
t_{PHL}	C_n to $\overline{F}$	Any	3.0	6.5	8.5	2.5	12.0	3.0	9.5	
t_{PLH}	Propagation Delay		3.0	5.7	7.5	2.5	9.0	3.0	8.5	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ or $\overline{G}$	Sum	3.0	5.8	7.5	2.5	9.5	3.0	8.5	
t_{PLH}	Propagation Delay		3.0	6.5	8.5	2.5	11.5	3.0	9.5	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to $\overline{G}$	Dif	3.0	7.3	9.5	2.5	11.0	3.0	10.5	
t_{PLH}	Propagation Delay		3.0	5.0	7.0	2.5	8.5	3.0	8.0	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to $\overline{P}$	Sum	3.0	5.5	7.5	3.0	9.5	3.0	8.5	
t_{PLH}	Propagation Delay		3.0	5.8	7.5	2.5	11.0	3.0	8.5	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to $\overline{P}$	Dif	4.0	6.5	8.5	3.0	11.0	4.0	9.5	
t_{PLH}	Propagation Delay		3.0	7.0	9.0	3.0	14.5	3.0	10.0	ns
t_{PHL}	$\overline{A}_i$ or $\overline{B}_i$ to $\overline{F}_i$	Sum	3.0	7.2	10.0	3.0	14.5	3.0	10.0	
t_{PLH}	Propagation Delay		3.0	8.2	11.0	3.0	17.5	3.0	12.0	ns
t_{PHL}	$\overline{A}_i$ or $\overline{B}_i$ to $\overline{F}_i$	Dif	3.0	5.0	11.0	3.0	14.5	3.0	12.0	
t_{PLH}	Propagation Delay		4.0	8.0	10.5	3.5	16.5	4.0	11.5	ns
t_{PHL}	Any $\overline{A}$ or $\overline{B}$ to Any $\overline{F}$	Sum	4.0	7.8	10.0	4.0	13.5	4.0	11.0	
t_{PLH}	Propagation Delay		4.5	9.4	12.0	3.5	17.5	4.5	13.0	ns
t_{PHL}	Any $\overline{A}$ or $\overline{B}$ to Any $\overline{F}$	Dif	3.5	9.4	12.0	3.0	14.0	3.5	13.0	
t_{PLH}	Propagation Delay		4.0	6.0	9.0	3.5	14.5	4.0	10.0	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to $\overline{F}$	Logic	4.0	6.0	10.0	3.0	15.5	4.0	11.0	
t_{PLH}	Propagation Delay		11.0	18.5	27.0	8.0	35.0	11.0	29.0	ns
t_{PHL}	$\overline{A}$ or $\overline{B}$ to A = B	Dif	6.0	9.8	12.5	5.5	21.0	6.0	13.5	

Physical Dimensions inches (millimeters) unless otherwise noted

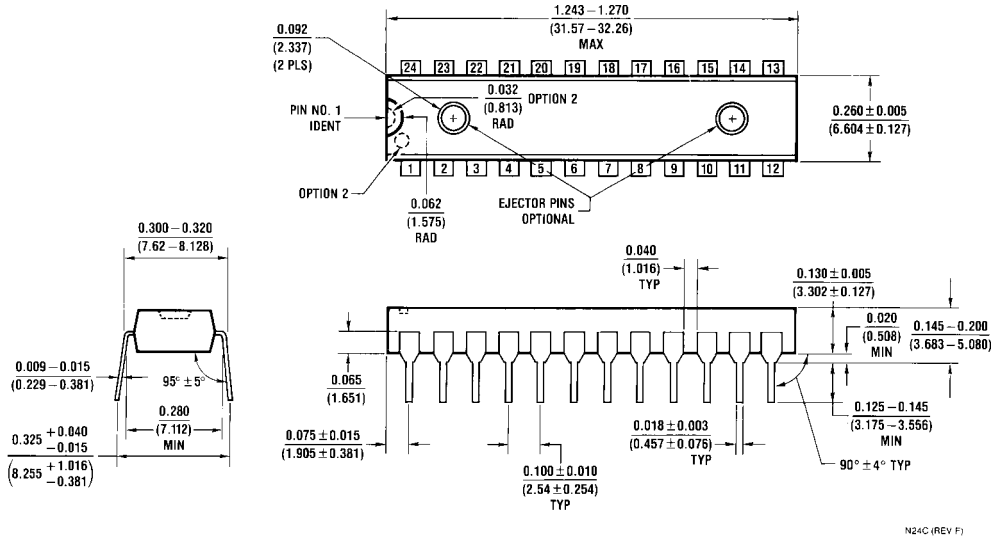


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
Package Number N24A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F182
Carry Lookahead Generator

General Description

The 74F182 is a high-speed carry lookahead generator. It is generally used with the 74F181 or 74F381 4-bit arithmetic logic units to provide high-speed lookahead over word lengths of more than four bits.

Features

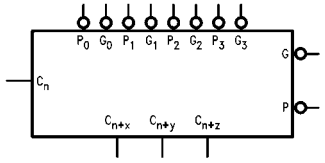
- Provides lookahead carries across a group of four ALUs
- Multi-level lookahead high-speed arithmetic operation over long word lengths

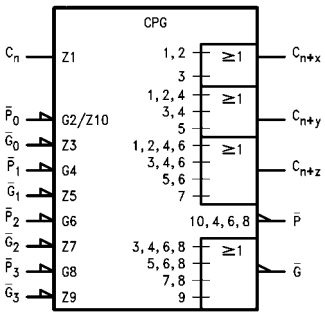
Ordering Code:

Order Number	Package Number	Package Description
74F182SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F182PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

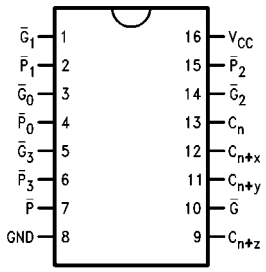
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
C_n	Carry Input	1.0/2.0	20 µA/–1.2 mA
$\overline{G}_0$, $\overline{G}_2$	Carry Generate Inputs (Active LOW)	1.0/14.0	20 µA/–8.4 mA
$\overline{G}_1$	Carry Generate Input (Active LOW)	1.0/16.0	20 µA/–9.6 mA
$\overline{G}_3$	Carry Generate Input (Active LOW)	1.0/8.0	20 µA/–4.8 mA
$\overline{P}_0$, $\overline{P}_1$	Carry Propagate Inputs (Active LOW)	1.0/8.0	20 µA/–4.8 mA
$\overline{P}_2$	Carry Propagate Input (Active LOW)	1.0/6.0	20 µA/–3.6 mA
$\overline{P}_3$	Carry Propagate Input (Active LOW)	1.0/4.0	20 µA/–2.4 mA
$C_{n+x} - C_{n+z}$	Carry Outputs	50/33.3	–1 mA/20 mA
$\overline{G}$	Carry Generate Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{P}$	Carry Propagate Output (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The 74F182 carry lookahead generator accepts up to four pairs of Active LOW Carry Propagate ($\overline{P}_0$–$\overline{P}_3$) and Carry Generate ($\overline{G}_0$–$\overline{G}_3$) signals and an Active HIGH Carry input (C_n) and provides anticipated Active HIGH carries (C_{n+x}, C_{n+y}, C_{n+z}) across four groups of binary adders. The 74F182 also has Active LOW Carry Propagate ($\overline{P}$) and Carry Generate ($\overline{G}$) outputs which may be used for further levels of lookahead. The logic equations provided at the outputs are:

$$C_{n+x} = G_0 + P_0 C_n$$

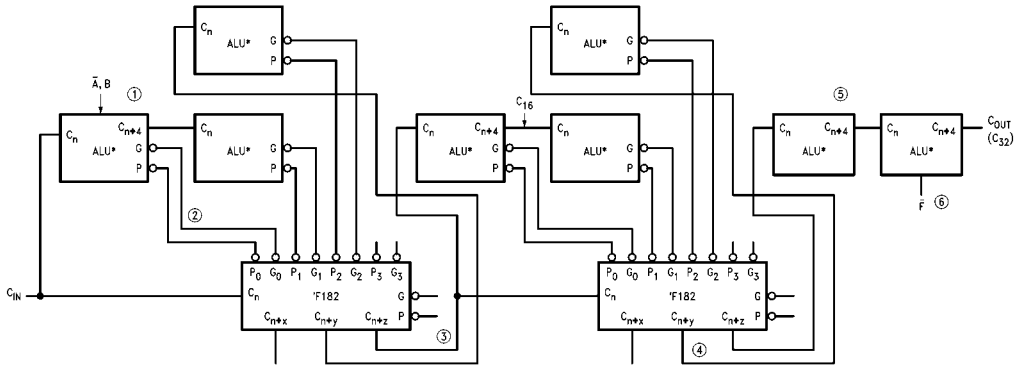
$$C_{n+y} = G_1 + P_1 G_0 + P_1 P_0 C_n$$

$$C_{n+z} = G_2 + P_2 G_1 + P_2 P_1 G_0 + P_2 P_1 P_0 C_n$$

$$G = \overline{G}_3 + \overline{P}_3 \overline{G}_2 + \overline{P}_3 \overline{P}_2 \overline{G}_1 + \overline{P}_3 \overline{P}_2 \overline{P}_1 \overline{G}_0$$

$$P = \overline{P}_2 \overline{P}_2 \overline{P}_1 \overline{P}_0$$

Also, the 74F182 can be used with binary ALUs in an active LOW or active HIGH input operand mode. The connections (Figure 1) to and from the ALU to the carry lookahead generator are identical in both cases. Carries are rippled between lookahead blocks. The critical speed path follows the circled numbers. There are several possible arrangements for the carry interconnects, but all achieve about the same speed. A 28-bit ALU is formed by dropping the last 74F181 or 74F381.



*ALUs may be either 74F181 or 74F381

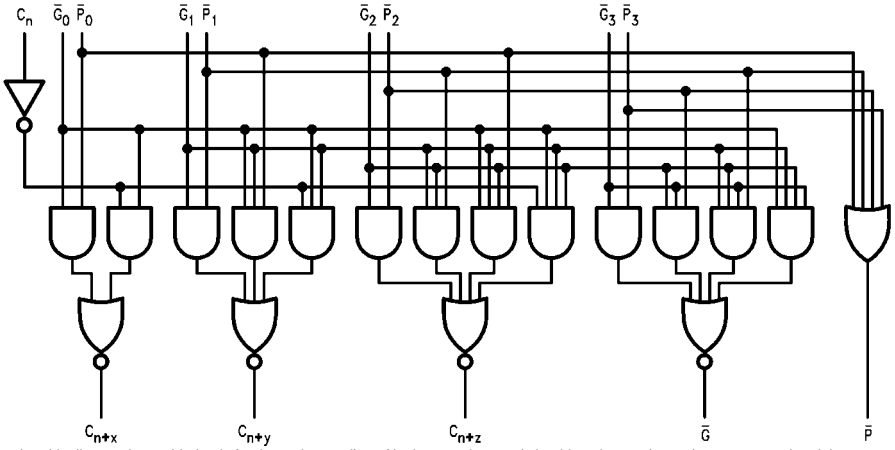
FIGURE 1. 32-Bit ALU with Rippled Carry between 16-Bit Lookahead ALUs

Truth Table

Inputs									Outputs				
C_n	$\overline{G}_0$	$\overline{P}_0$	$\overline{G}_1$	$\overline{P}_1$	$\overline{G}_2$	$\overline{P}_2$	$\overline{G}_3$	$\overline{P}_3$	C_{n+x}	C_{n+y}	C_{n+z}	$\overline{G}$	$\overline{P}$
X	H	H							L				
L	H	X							L				
X	L	X							H				
H	X	L							H				
X	X	X	H	H						L			
X	H	H	H	X						L			
L	H	X	H	X						L			
X	X	X	L	X						H			
X	L	X	X	L						H			
H	X	L	X	L						H			
X	X	X	X	X	H	H					L		
X	X	X	H	H	H	X					L		
X	H	H	H	X	H	X					L		
L	H	X	H	X	H	X					L		
X	X	X	X	X	L	X					H		
X	X	X	L	X	X	L					H		
X	L	X	X	L	X	L					H		
H	X	L	X	L	X	L					H		
	X		X	X	X	X	H	H				H	
	X		X	X	H	H	H	X				H	
	X		H	H	H	X	H	X				H	
	H		H	X	H	X	H	X				H	
	X		X	X	X	X	L	X				L	
	X		X	X	L	X	X	L				L	
	X		L	X	X	L	X	L				L	
	L		X	L	X	L	X	L				L	
		H		X		X		X					H
		X		H		X		X					H
		X		X		H		X					H
		X		X		X		H					H
		L		L		L		L					L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

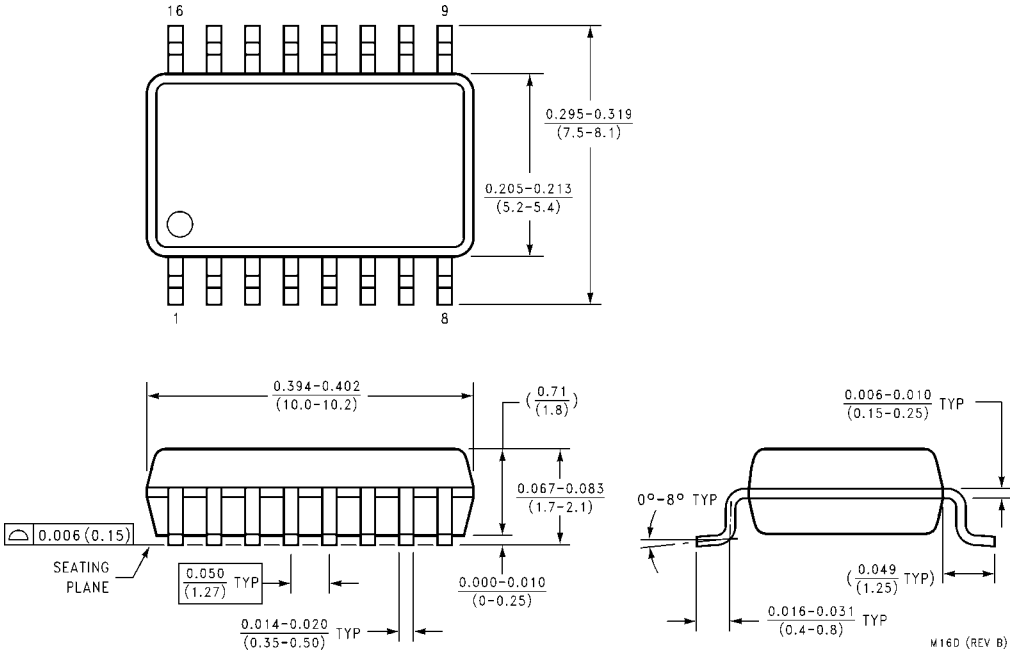
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.2	mA	Max	V_{IN} = 0.5V (C_n)
					−2.4			V_{IN} = 0.5V ($\overline{P}_3$)
					−3.6			V_{IN} = 0.5V ($\overline{P}_2$)
					−4.8			V_{IN} = 0.5V ($\overline{G}_3$, $\overline{P}_0$, $\overline{P}_1$)
					−8.4			V_{IN} = 0.5V ($\overline{G}_0$, $\overline{G}_2$)
					−9.6			V_{IN} = 0.5V ($\overline{G}_1$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			18.4	28.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			23.5	36.0	mA	Max	V_O = LOW

AC Electrical Characteristics

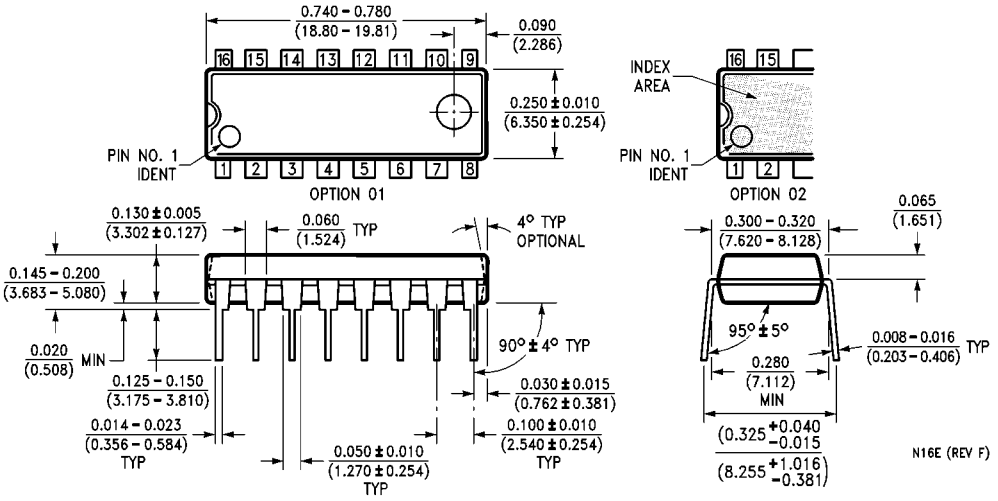
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	6.6	8.5	3.0	12.0	3.0	9.5	ns
t_{PHL}	C_n to C_{n+x}, C_{n+y}, C_{n+z}	3.0	6.8	9.0	3.0	11.0	3.0	10.0	
t_{PLH}	Propagation Delay	2.5	6.2	8.0	2.5	11.0	2.5	9.0	ns
t_{PHL}	$\overline{P}_0$, $\overline{P}_1$, or $\overline{P}_2$ to	1.5	3.7	5.0	1.0	7.0	1.5	6.0	
	C_{n+x}, C_{n+y}, or C_{n+z}								
t_{PLH}	Propagation Delay	2.5	6.5	8.5	2.5	11.0	2.5	9.5	ns
t_{PHL}	$\overline{G}_0$, $\overline{G}_1$, or $\overline{G}_2$ to	1.5	3.9	5.2	1.0	7.0	1.5	6.0	
	C_{n+x}, C_{n+y}, or C_{n+z}								
t_{PLH}	Propagation Delay	3.0	7.9	10.0	3.0	12.0	3.0	11.0	ns
t_{PHL}	$\overline{P}_1$, $\overline{P}_2$, or $\overline{P}_3$ to $\overline{G}$	3.0	6.0	8.0	2.5	10.0	3.0	9.0	
t_{PLH}	Propagation Delay	3.0	8.3	10.5	3.0	12.0	3.0	11.5	ns
t_{PHL}	$\overline{G}_n$ to $\overline{G}$	3.0	5.7	7.5	2.5	10.0	3.0	8.5	
t_{PLH}	Propagation Delay	3.0	5.7	7.5	2.5	10.0	3.0	8.5	ns
t_{PHL}	$\overline{P}_n$ to $\overline{P}$	2.5	4.1	5.5	2.5	8.0	2.5	6.5	

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F189
64-Bit Random Access Memory with 3-STATE Outputs

General Description

The F189 is a high-speed 64-bit RAM organized as a 16-word by 4-bit array. Address inputs are buffered to minimize loading and are fully decoded on-chip. The outputs are 3-STATE and are in the high impedance state whenever the Chip Select ($\overline{CS}$) input is HIGH. The outputs are active only in the Read mode and the output data is the complement of the stored data.

Features

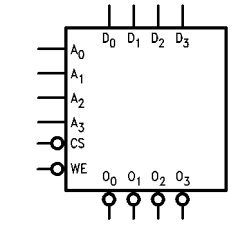
- 3-STATE outputs for data bus applications
- Buffered inputs minimize loading
- Address decoding on-chip
- Diode clamped inputs minimize ringing

Ordering Code:

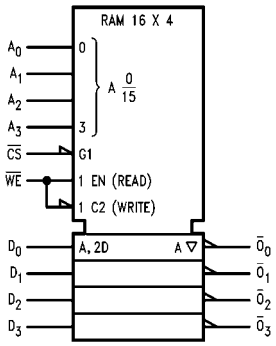
Order Number	Package Number	Package Description
74F189SC	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74F189SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F189PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix "X" to the ordering code.

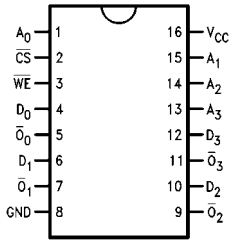
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

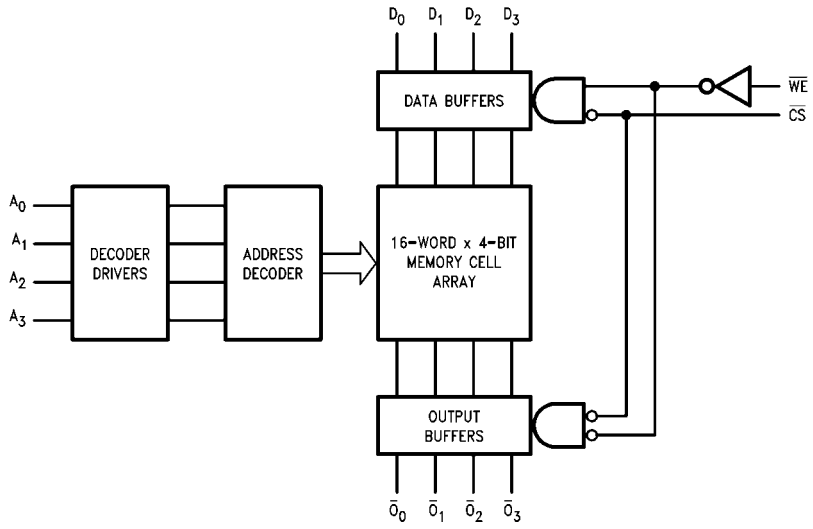
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	Address Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/1.0	20 µA/–1.2 mA
$\overline{WE}$	Write Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
D_0–D_3	Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_0$–$\overline{O}_3$	Inverted Data Outputs	150/40 (33.3)	–3.0 mA/24 mA (20 mA)

Function Table

Inputs		Operation	Condition of Outputs
$\overline{CS}$	$\overline{WE}$		
L	L	Write	High Impedance
L	H	Read	Complement of Stored Data
H	X	Inhibit	High Impedance

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (except $\overline{CS}$)
					−1.2			V_{IN} = 0.5V ($\overline{CS}$)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			37	55	mA	Max	V_O = HIGH Z

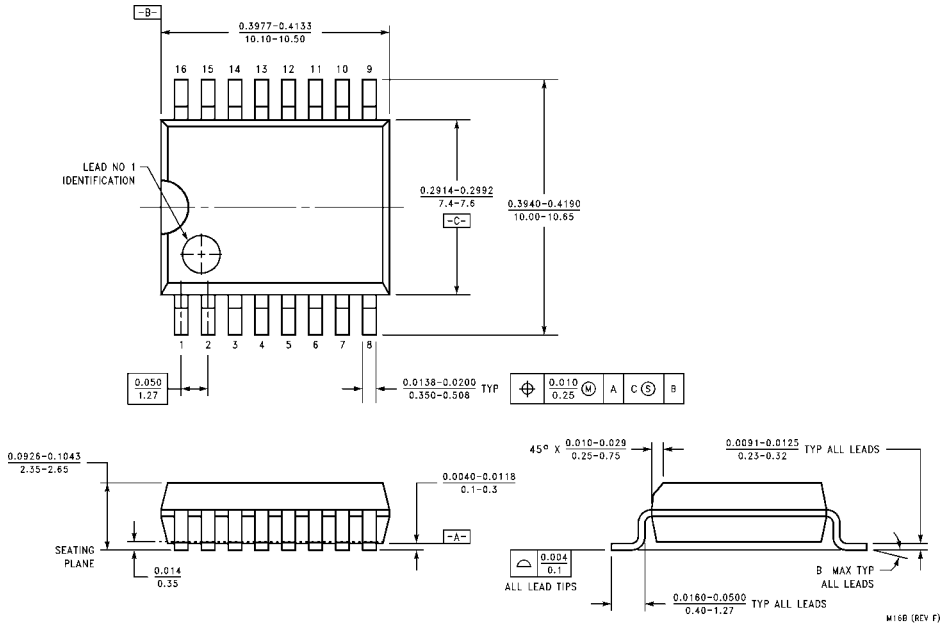
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Access Time, HIGH or LOW	10.0	18.5	26.0	9.0	32.0	10.0	27.0	ns
t_{PHL}	A_n to $\overline{O}_n$	8.0	13.5	19.0	8.0	23.0	8.0	20.0	
t_{PZH}	Access Time, HIGH or LOW	3.5	6.0	8.5	3.5	10.5	3.5	9.5	ns
t_{PZL}	$\overline{CS}$ to $\overline{O}_n$	5.0	9.0	13.0	5.0	15.0	5.0	14.0	
t_{PHZ}	Disable Time, HIGH or LOW	2.0	4.0	6.0	2.0	8.0	2.0	7.0	ns
t_{PLZ}	$\overline{CS}$ to $\overline{O}_n$	3.0	5.5	8.0	2.5	10.0	3.0	9.0	
t_{PZH}	Write Recovery Time,	6.5	15.0	28.0	6.5	37.5	6.5	29.0	ns
t_{PZL}	HIGH or LOW $\overline{WE}$ to $\overline{O}_n$	6.5	11.0	15.5	6.5	17.5	6.5	16.5	
t_{PHZ}	Disable Time, HIGH or LOW	4.0	7.0	10.0	3.5	12.0	4.0	11.0	ns
t_{PLZ}	$\overline{WE}$ to $\overline{O}_n$	5.0	9.0	13.0	5.0	15.0	5.0	14.0	

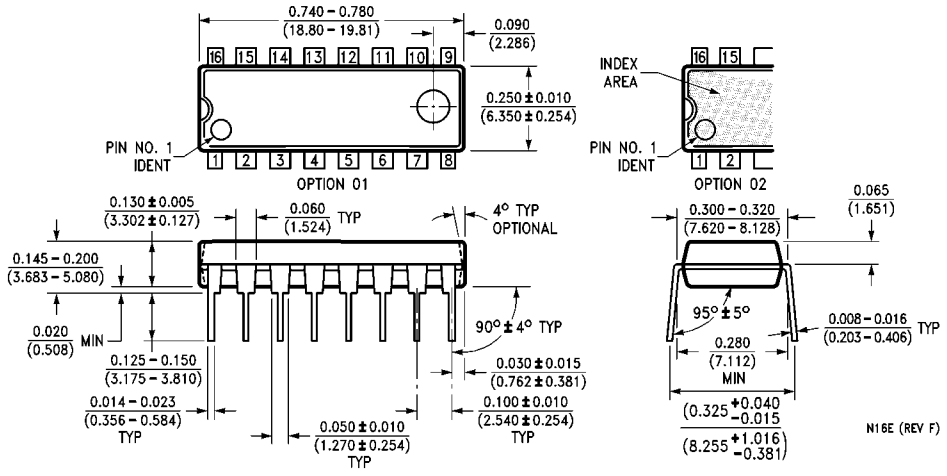
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	0		0		0		ns
$t_S(L)$	A_n to $\overline{WE}$	0		0		0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	A_n to $\overline{WE}$	2.0		2.0		2.0		
$t_S(H)$	Setup Time, HIGH or LOW	10.0		11.0		10.0		ns
$t_S(L)$	D_n to $\overline{WE}$	10.0		11.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		2.0		0		
$t_H(L)$	D_n to $\overline{WE}$	0		2.0		0		
$t_S(L)$	Setup Time, LOW	0		0		0		ns
	$\overline{CS}$ to $\overline{WE}$							
$t_H(L)$	Hold Time, LOW	6.0		7.5		6.0		
	$\overline{CS}$ to $\overline{WE}$							
$t_W(L)$	$\overline{WE}$ Pulse Width, LOW	6.0		15.0		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

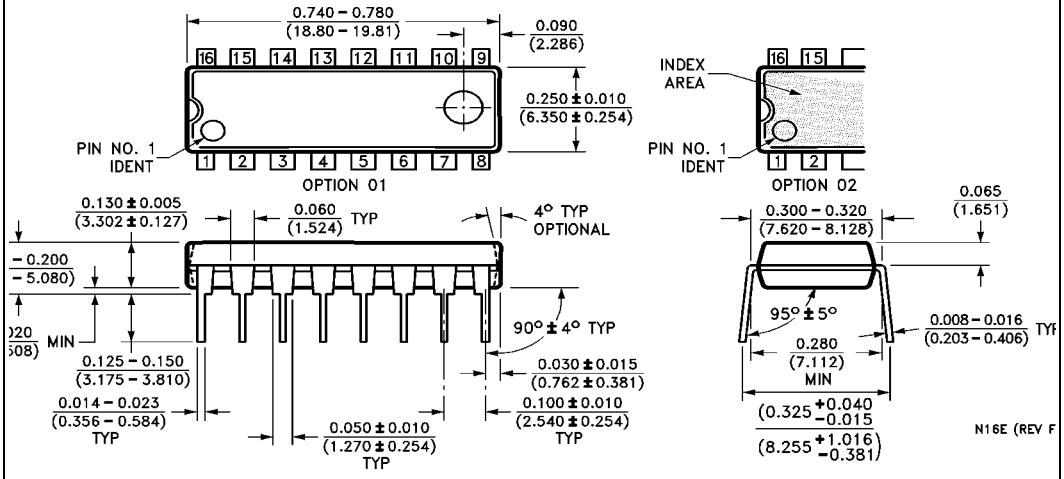


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS013, 0.300" Wide Body
Package Number M16B



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-OO1, 0.300" Wide
Package Number N16E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F190
Up/Down Decade Counter with Preset and Ripple Clock

General Description

The 74F190 is a reversible BCD (8421) decade counter featuring synchronous counting and asynchronous presetting. The preset feature allows the 74F190 to be used in programmable dividers. The Count Enable input, the Terminal Count output and the Ripple Clock output make possible a variety of methods of implementing multistage counters. In the counting modes, state changes are initiated by the rising edge of the clock.

Features

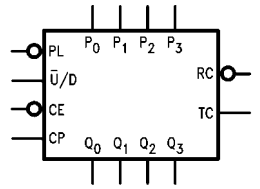
- High-speed—125 MHz typical count frequency
- Synchronous counting
- Asynchronous parallel load
- Cascadable

Ordering Code:

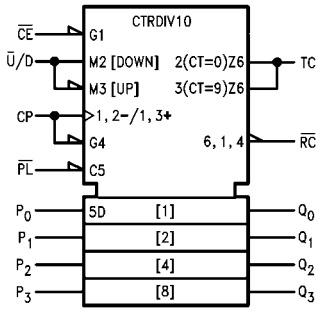
Order Number	Package Number	Package Description
74F190SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F190PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

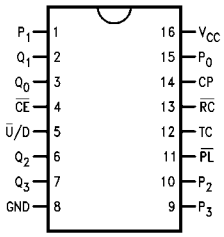
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{CE}$	Count Enable Input (Active LOW)	1.0/3.0	20 μA/–1.8 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{PL}$	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{U}$/D	Up/Down Count Control Input	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
$\overline{RC}$	Ripple Clock Output (Active LOW)	50/33.3	–1 mA/20 mA
TC	Terminal Count Output (Active HIGH)	50/33.3	–1 mA/20 mA

Functional Description

The 74F190 is a synchronous up/down BCD decade counter containing four edge-triggered flip-flops, with internal gating and steering logic to provide individual preset, count-up and count-down operations. It has an asynchronous parallel load capability permitting the counter to be preset to any desired number. When the Parallel Load ($\overline{PL}$) input is LOW, information present on the Parallel Data inputs (P_0–P_3) is loaded into the counter and appears on the Q outputs. This operation overrides the counting functions, as indicated in the Mode Select Table. A HIGH signal on the $\overline{CE}$ input inhibits counting. When $\overline{CE}$ is LOW, internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The direction of counting is determined by the $\overline{U}$/D input signal, as indicated in the Mode Select Table, $\overline{CE}$ and $\overline{U}$/D can be changed with the clock in either state, provided only that the recommended setup and hold times are observed.

Two types of outputs are provided as overflow/underflow indicators. The Terminal Count (TC) output is normally LOW and goes HIGH when a circuit reaches zero in the count-down mode or reaches 9 in the count-up mode. The TC output will then remain HIGH until a state change occurs, whether by counting or presetting or until $\overline{U}$/D is changed. The TC output should not be used as a clock signal because it is subject to decoding spikes. The TC signal is also used internally to enable the Ripple Clock ($\overline{RC}$) output. The $\overline{RC}$ output is normally HIGH. When $\overline{CE}$ is LOW and TC is HIGH, the $\overline{RC}$ output will go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again. This feature simplifies the design of multistage counters. For a discussion and illustrations of the various methods of implementing multistage counters, please see the 74F191 data sheet.

$\overline{RC}$ Truth Table

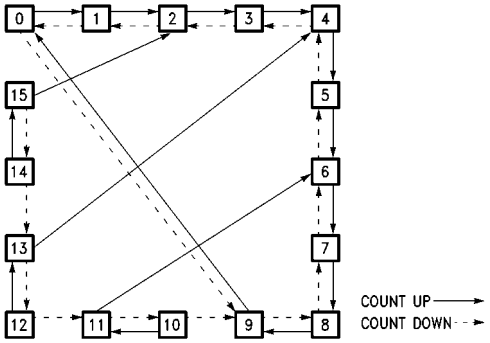
Inputs			Output
$\overline{CE}$	TC*	CP	$\overline{RC}$
L	H	⊓	⊓
H	X	X	H
X	L	X	H

Mode Select Table

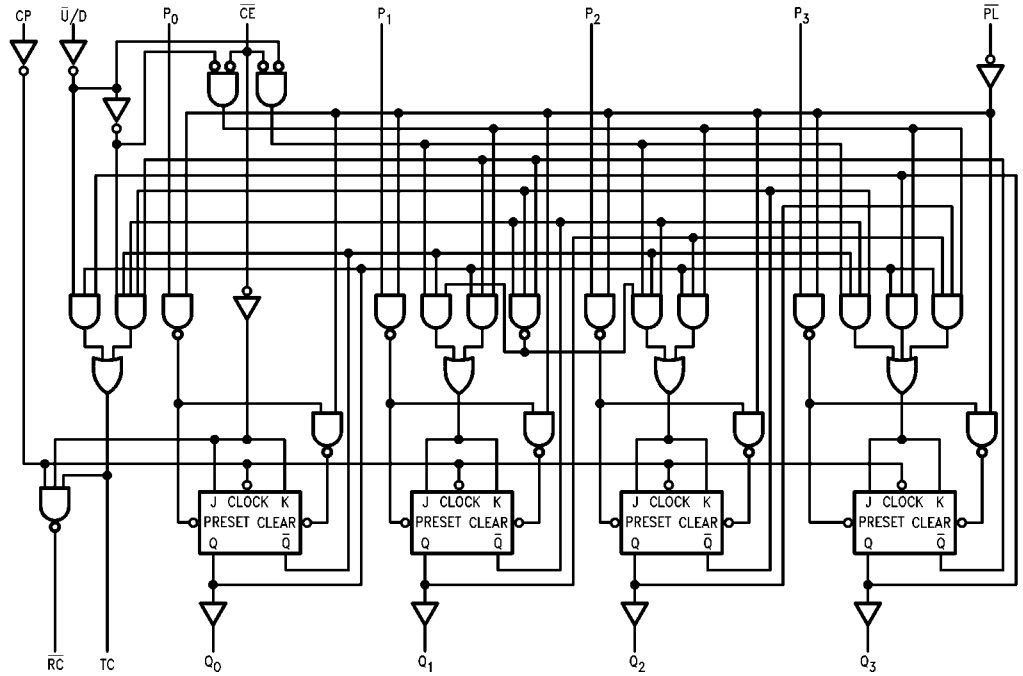
Inputs				Mode
$\overline{PL}$	$\overline{CE}$	$\overline{U}$/D	CP	
H	L	L	⌐	Count Up
H	L	H	⌐	Count Down
L	X	X	X	Preset (Asyn.)
H	H	X	X	No Change (Hold)

*TC is generated internally
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
⊓ = LOW Pulse

State Diagram



Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V, except $\overline{CE}$
				−1.8			V_{IN} = 0.5V, $\overline{CE}$
I_{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V_{OUT} = 0V
I_{CCL}	Power Supply Current		38	55	mA	Max	V_O = LOW

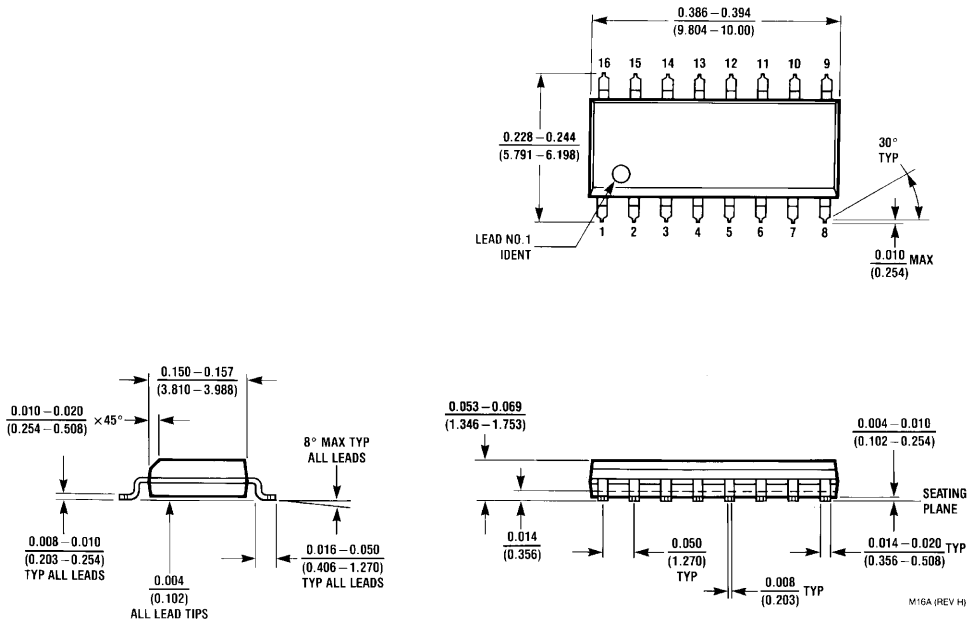
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	125		75		90		MHz
t_{PLH}	Propagation Delay	3.0	5.5	7.5	3.0	9.5	3.0	8.5	ns
t_{PHL}	CP to Q_n	5.0	8.5	11.0	5.0	13.5	5.0	12.0	
t_{PLH}	Propagation Delay	6.0	10.0	13.0	6.0	16.5	6.0	14.0	ns
t_{PHL}	CP to TC	5.0	8.5	11.0	5.0	13.5	5.0	12.0	
t_{PLH}	Propagation Delay	3.0	5.5	7.5	3.0	9.5	3.0	8.5	ns
t_{PHL}	CP to $\overline{RC}$	3.0	5.0	7.0	3.0	9.0	3.0	8.0	
t_{PLH}	Propagation Delay	3.0	5.0	7.0	3.0	9.0	3.0	8.0	ns
t_{PHL}	$\overline{CE}$ to $\overline{RC}$	3.0	5.5	7.0	3.0	9.0	3.0	8.0	
t_{PLH}	Propagation Delay	7.0	11.0	18.0	7.0	22.0	7.0	20.0	ns
t_{PHL}	$\overline{U}$ /D to $\overline{RC}$	5.5	9.0	12.0	5.5	14.0	5.5	13.0	
t_{PLH}	Propagation Delay	4.0	7.0	10.0	4.0	13.5	4.0	11.0	
t_{PHL}	$\overline{U}$ /D to $\overline{TC}$	4.0	6.5	10.0	4.0	12.5	4.0	11.0	
t_{PLH}	Propagation Delay	3.0	4.5	7.0	3.0	9.0	3.0	8.0	ns
t_{PHL}	P_n to Q_n	6.0	10.0	13.0	6.0	16.0	6.0	14.0	
t_{PLH}	Propagation Delay	5.0	8.5	11.0	5.0	13.0	5.0	12.0	ns
t_{PHL}	$\overline{PL}$ to Q_n	5.5	9.0	12.0	5.5	14.5	5.5	13.0	

AC Operating Requirements

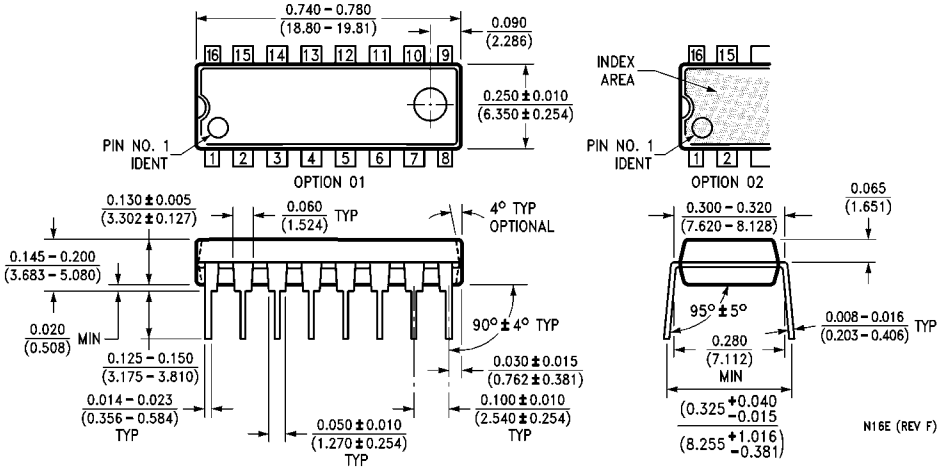
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.5		6.0		5.0		ns
$t_S(L)$	P_n to $\overline{PL}$	4.5		6.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	P_n to $\overline{PL}$	2.0		2.0		2.0		
$t_S(L)$	Setup Time, LOW	10.0		10.5		10.0		ns
	$\overline{CE}$ to CP							
$t_H(L)$	Hold Time, LOW	0		0		0		
	$\overline{CE}$ to CP							
$t_S(H)$	Setup Time, HIGH or LOW	12.0		12.0		12.0		ns
$t_S(L)$	$\overline{U}$ /D to CP	12.0		12.0		12.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	$\overline{U}$ /D to CP	0		0		0		
$t_W(L)$	$\overline{PL}$ Pulse Width, LOW	6.0		8.5		6.0		ns
$t_W(L)$	CP Pulse Width, LOW	5.0		7.0		5.0		ns
t_{REC}	Recovery Time $\overline{PL}$ to CP	6.0		7.5		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F191
Up/Down Binary Counter with Preset and Ripple Clock

General Description

The 74F191 is a reversible modulo-16 binary counter featuring synchronous counting and asynchronous presetting. The preset feature allows the 74F191 to be used in programmable dividers. The Count Enable input, the Terminal Count output and Ripple Clock output make possible a variety of methods of implementing multistage counters. In the counting modes, state changes are initiated by the rising edge of the clock.

Features

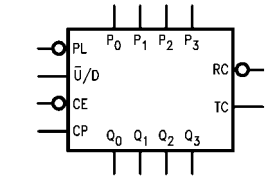
- High-Speed—125 MHz typical count frequency
- Synchronous counting
- Asynchronous parallel load
- Cascadable

Ordering Code:

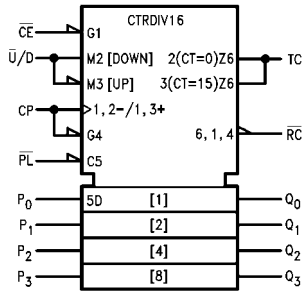
Order Number	Package Number	Package Description
74F191SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F191SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F191PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

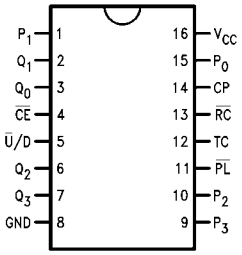
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{CE}$	Count Enable Input (Active LOW)	1.0/3.0	20 µA/–1.8 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{PL}$	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{U}$/D	Up/Down Count Control Input	1.0/1.0	20 µA/–0.6 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
$\overline{RC}$	Ripple Clock Output (Active LOW)	50/33.3	–1 mA/20 mA
TC	Terminal Count Output (Active HIGH)	50/33.3	–1 mA/20 mA

Functional Description

The 74F191 is a synchronous up/down 4-bit binary counter. It contains four edge-triggered flip-flops, with internal gating and steering logic to provide individual preset, count-up and count-down operations.

Each circuit has an asynchronous parallel load capability permitting the counter to be preset to any desired number. When the Parallel Load ($\overline{PL}$) input is LOW, information present on the Parallel Data inputs (P_0–P_3) is loaded into the counter and appears on the Q outputs. This operation overrides the counting functions, as indicated in the Mode Select Table.

A HIGH signal on the $\overline{CE}$ input inhibits counting. When $\overline{CE}$ is LOW, internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The direction of counting is determined by the $\overline{U}$/D input signal, as indicated in the Mode Select Table. $\overline{CE}$ and $\overline{U}$/D can be changed with the clock in either state, provided only that the recommended setup and hold times are observed.

Two types of outputs are provided as overflow/underflow indicators. The Terminal Count (TC) output is normally LOW and goes HIGH when a circuit reaches zero in the count-down mode or reaches 15 in the count-up mode. The TC output will then remain HIGH until a state change occurs, whether by counting or presetting or until $\overline{U}$/D is changed. The TC output should not be used as a clock signal because it is subject to decoding spikes.

The TC signal is also used internally to enable the Ripple Clock ($\overline{RC}$) output. The $\overline{RC}$ output is normally HIGH. When $\overline{CE}$ is LOW and TC is HIGH, the $\overline{RC}$ output will go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again. This feature simplifies the design of multistage counters, as indicated in Figure 1 and Figure 2. In Figure 1, each $\overline{RC}$ output is used as the clock input for the next higher stage. This configuration is particularly advantageous when the clock source has a limited drive capability, since it drives only the first stage. To prevent counting in all stages it is only necessary to inhibit the first stage, since a HIGH signal on $\overline{CE}$ inhibits the $\overline{RC}$ output pulse, as indicated in the $\overline{RC}$ Truth Table. A disadvantage of this configuration, in some applications, is the timing skew between state changes in the first and last stages. This represents the cumulative delay of the clock as it ripples through the preceding stages.

A method of causing state changes to occur simultaneously in all stages is shown in Figure 2. All clock inputs are driven in parallel and the $\overline{RC}$ outputs propagate the carry/borrow signals in ripple fashion. In this configuration the LOW state duration of the clock must be long enough to allow the negative-going edge of the carry/borrow signal to ripple through to the last stage before the clock goes HIGH. There is no such restriction on the HIGH state duration of the clock, since the $\overline{RC}$ output of any device goes HIGH shortly after its CP input goes HIGH.

The configuration shown in Figure 3 avoids ripple delays and their associated restrictions. The $\overline{CE}$ input for a given stage is formed by combining the TC signals from all the preceding stages. Note that in order to inhibit counting an enable signal must be included in each carry gate. The simple inhibit scheme of Figure 1 and Figure 2 doesn't apply, because the TC output of a given stage is not affected by its own $\overline{CE}$.

Mode Select Table

Inputs				Mode
$\overline{PL}$	$\overline{CE}$	$\overline{U}$/D	CP	
H	L	L	⌐	Count Up
H	L	H	⌐	Count Down
L	X	X	X	Preset (Asyn.)
H	H	X	X	No Change (Hold)

$\overline{RC}$ Truth Table

Inputs			Output
$\overline{CE}$	TC*	CP	$\overline{RC}$
L	H	⌐‾⌐	⌐‾⌐
H	X	X	H
X	L	X	H

*TC is generated internally
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
⌐‾⌐ = LOW Pulse

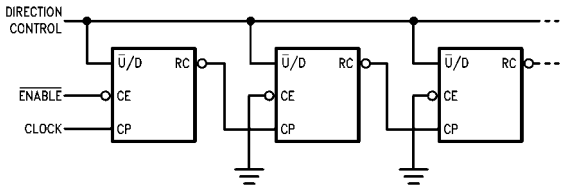


FIGURE 1. n-Stage Counter Using Ripple Clock

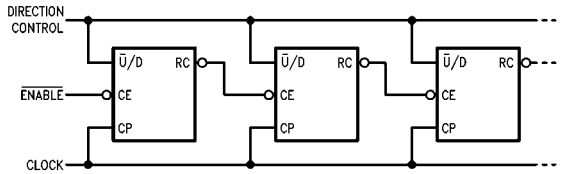


FIGURE 2. Synchronous n-Stage Counter Using Ripple Carry/Borrow

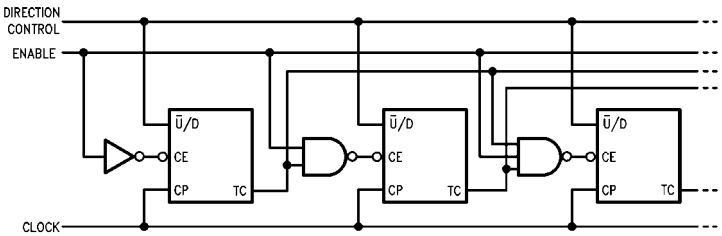
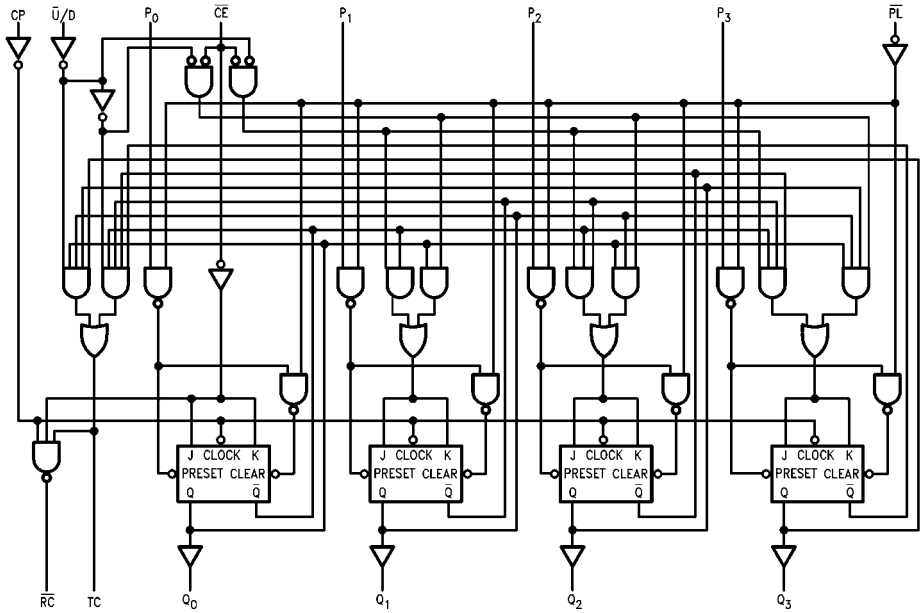


FIGURE 3. Synchronous n-Stage Counter with Gated Carry/Borrow

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (except $\overline{CE}$)
				−1.8			V_{IN} = 0.5V ($\overline{CE}$)
I_{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current		38	55	mA	Max	

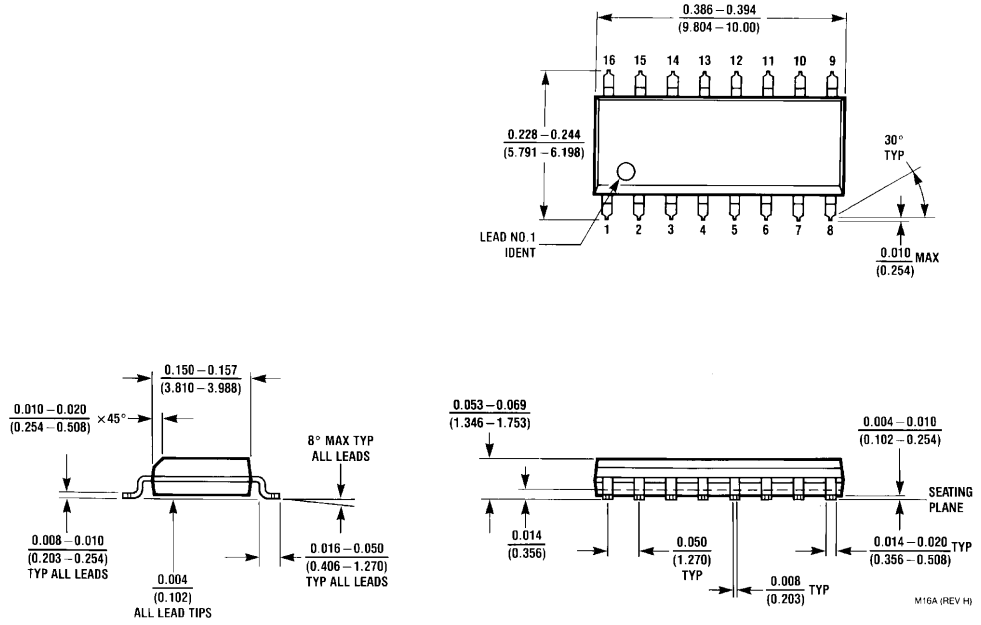
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	100	125		75		90		MHz
t_{PLH}	Propagation Delay	3.0	5.5	7.5	3.0	9.5	3.0	8.5	ns
t_{PHL}	CP to Q_n	5.0	8.5	11.0	5.0	13.5	5.0	12.0	
t_{PLH}	Propagation Delay	6.0	10.0	13.0	6.0	16.5	6.0	14.0	
t_{PHL}	CP to TC	5.0	8.5	11.0	5.0	13.5	5.0	12.0	
t_{PLH}	Propagation Delay	3.0	5.5	7.5	3.0	9.5	3.0	8.5	ns
t_{PHL}	CP to $\overline{RC}$	3.0	5.0	7.0	3.0	9.0	3.0	8.0	
t_{PLH}	Propagation Delay	3.0	5.0	7.0	3.0	9.0	3.0	8.0	
t_{PHL}	$\overline{CE}$ to $\overline{RC}$	3.0	5.5	7.0	3.0	9.0	3.0	8.0	
t_{PLH}	Propagation Delay	7.0	11.0	18.0	7.0	22.0	7.0	20.0	ns
t_{PHL}	$\overline{U}$/D to $\overline{RC}$	5.5	9.0	12.0	5.5	14.0	5.5	13.0	
t_{PLH}	Propagation Delay	4.0	7.0	10.0	4.0	13.5	4.0	11.0	
t_{PHL}	$\overline{U}$/D to TC	4.0	6.5	10.0	4.0	12.5	4.0	11.0	
t_{PLH}	Propagation Delay	3.0	4.5	7.0	3.0	9.0	3.0	8.0	ns
t_{PHL}	P_n to Q_n	6.0	10.0	13.0	6.0	16.0	6.0	14.0	
t_{PLH}	Propagation Delay	5.0	8.5	11.0	5.0	13.0	5.0	12.0	ns
t_{PHL}	$\overline{PL}$ to Q_n	5.5	9.0	12.0	5.5	14.5	5.5	13.0	
t_{PLH}	Propagation Delay	5.0		14.0			5.0	15.0	ns
t_{PHL}	P_n to TC	6.5		13.0			6.0	14.0	
t_{PLH}	Propagation Delay	6.5		19.0			6.5	20.0	ns
t_{PHL}	P_n to $\overline{RC}$	6.0		14.0			6.0	15.0	
t_{PLH}	Propagation Delay	8.0		16.5			8.0	17.5	ns
t_{PHL}	$\overline{PL}$ to TC	6.0		13.5			6.0	14.5	
t_{PLH}	Propagation Delay	10.0		20.0			10.0	21.0	ns
t_{PHL}	$\overline{PL}$ to $\overline{RC}$	9.0		15.5			9.0	16.0	

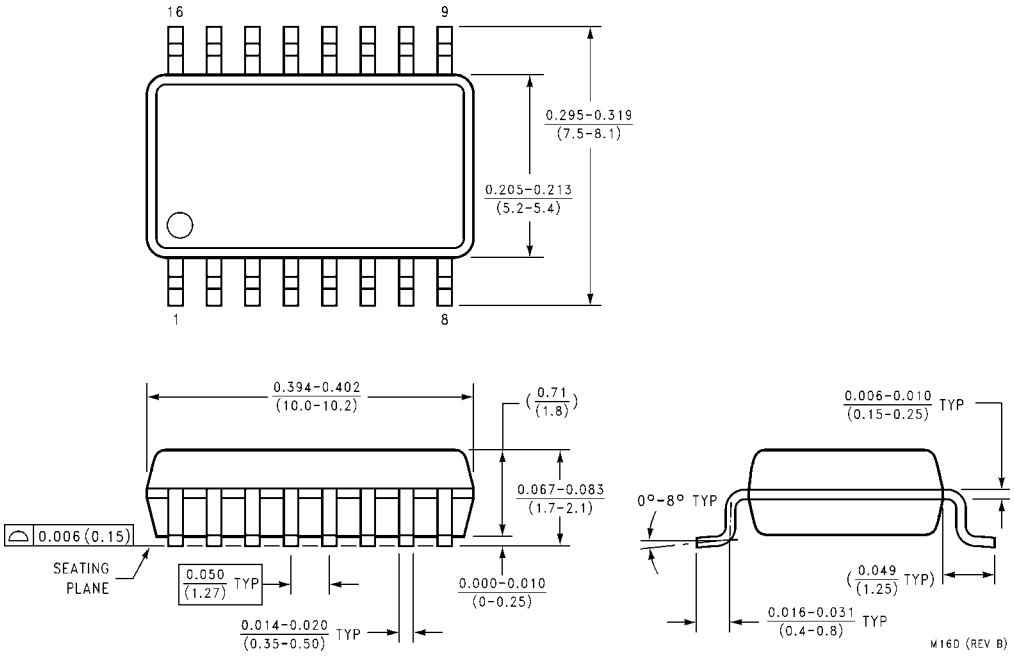
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.5		6.0		5.0		ns
$t_S(L)$	P_n to $\overline{PL}$	4.5		6.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	P_n to $\overline{PL}$	2.0		2.0		2.0		
$t_S(L)$	Setup Time LOW	10.0		10.5		10.0		ns
	$\overline{CE}$ to CP							
$t_H(L)$	Hold Time LOW	0		0		0		
	$\overline{CE}$ to CP							
$t_S(H)$	Setup Time, HIGH or LOW	12.0		12.0		12.0		ns
$t_S(L)$	$\overline{U}$/D to CP	12.0		12.0		12.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	$\overline{U}$/D to CP	0		0		0		
$t_W(L)$	$\overline{PL}$ Pulse Width LOW	6.0		8.5		6.0		ns
$t_W(L)$	CP Pulse Width LOW	5.0		7.0		5.0		ns
t_{REC}	Recovery Time	6.0		7.5		6.0		ns
	$\overline{PL}$ to CP							

Physical Dimensions inches (millimeters) unless otherwise noted

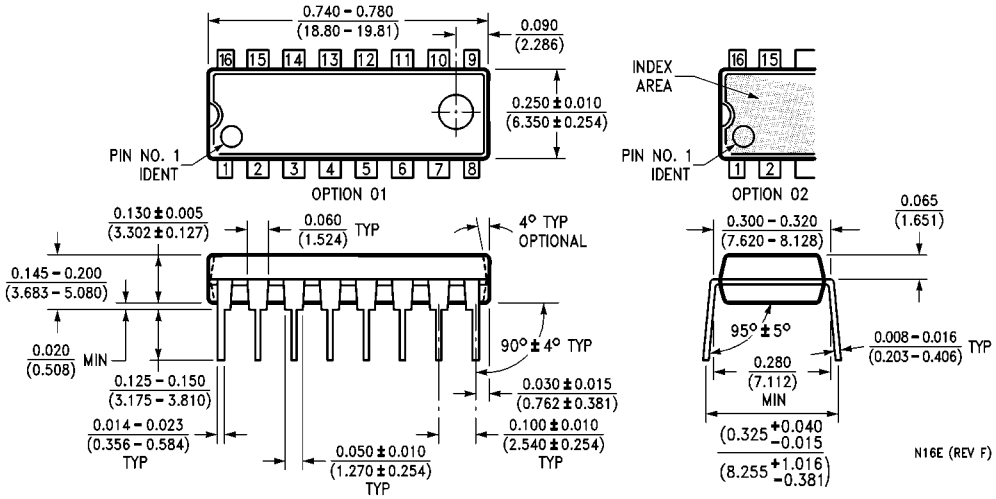


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised March 1999

74F192
Up/Down Decade Counter with Separate Up/Down Clocks

General Description

The 74F192 is an up/down BCD decade (8421) counter. Separate Count Up and Count Down Clocks are used, and in either counting mode the circuits operate synchronously. The outputs change state synchronously with the LOW-to-HIGH transitions on the clock inputs.

Separate Terminal Count Up and Terminal Count Down outputs are used as the clocks for a subsequent stage without extra logic, thus simplifying multistage counter designs. Individual preset inputs allow the circuit to be used as a programmable counter. Both the Parallel Load ($\overline{PL}$) and the Master Reset (MR) inputs asynchronously override the clocks.

Features

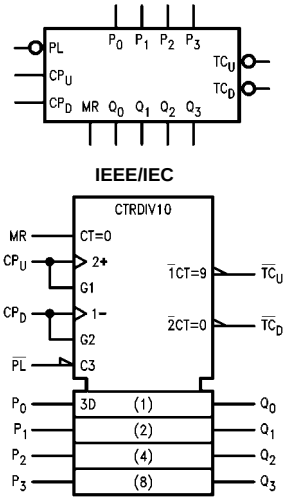
- Guaranteed 4000V minimum ESD protection

Ordering Code:

Order Number	Package Number	Package Description
74F192SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F192PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

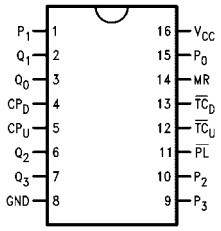
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
CP_U	Count Up Clock Input (Active Rising Edge)	1.0/3.0	20 µA/–1.8 mA
CP_D	Count Down Clock Input (Active Rising Edge)	1.0/3.0	20 µA/–1.8 mA
MR	Asynchronous Master Reset Input (Active HIGH)	1.0/1.0	20 µA/–0.6 mA
$\overline{PL}$	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
$\overline{TC}_D$	Terminal Count Down (Borrow) Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{TC}_U$	Terminal Count Up (Carry) Output (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The 74F192 is an asynchronously presettable decade counter. It contains four edge-triggered flip-flops, with internal gating and steering logic to provide master reset, individual preset, count up and count down operations.

A LOW-to-HIGH transition on the CP input to each flip-flop causes the output to change state. Synchronous switching, as opposed to ripple counting, is achieved by driving the steering gates of all stages from a common Count Up line and a common Count Down line, thereby causing all state changes to be initiated simultaneously. A LOW-to-HIGH transition on the Count Up input will advance the count by one; a similar transition on the Count Down input will decrease the count by one. While counting with one clock input, the other should be held HIGH, as indicated in the Function Table. Otherwise, the circuit will either count by twos or not at all, depending on the state of the first flip-flop, which cannot toggle as long as either clock input is LOW.

The Terminal Count Up ($\overline{TC}_U$) and Terminal Count Down ($\overline{TC}_D$) outputs are normally HIGH. When the circuit has reached the maximum count state 9, the next HIGH-to-LOW transition of the Count Up Clock will cause $\overline{TC}_U$ to go LOW. $\overline{TC}_U$ will stay LOW until CP_U goes HIGH again, thus effectively repeating the Count Up Clock, but delayed by two gate delays. Similarly, the $\overline{TC}_D$ output will go LOW when the circuit is in the zero state and the Count Down Clock goes LOW. Since the $\overline{TC}$ outputs repeat the clock waveforms, they can be used as the clock input signals to the next higher order circuit in a multistage counter.

$$\overline{TC}_U = Q_0 \bullet Q_3 \bullet \overline{CP}_U$$

$$\overline{TC}_D = \overline{Q}_0 \bullet \overline{Q}_1 \bullet \overline{Q}_2 \bullet \overline{Q}_3 \bullet \overline{CP}_D$$

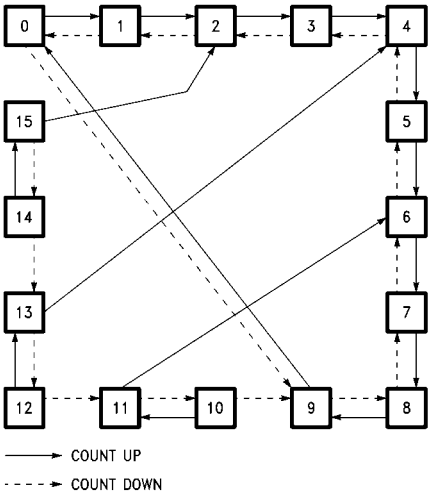
The 74F192 has an asynchronous parallel load capability permitting the counter to be preset. When the Parallel Load ($\overline{PL}$) and the Master Reset (MR) inputs are LOW, information present on the Parallel Data input (P_0–P_3) is loaded into the counter and appears on the outputs regardless of the conditions of the clock inputs. A HIGH signal on the Master Reset input will disable the preset gates, override both clock inputs, and latch each Q output in the LOW state. If one of the clock inputs is LOW during and after a reset or load operation, the next LOW-to-HIGH transition of that clock will be interpreted as a legitimate signal and will be counted.

Function Table

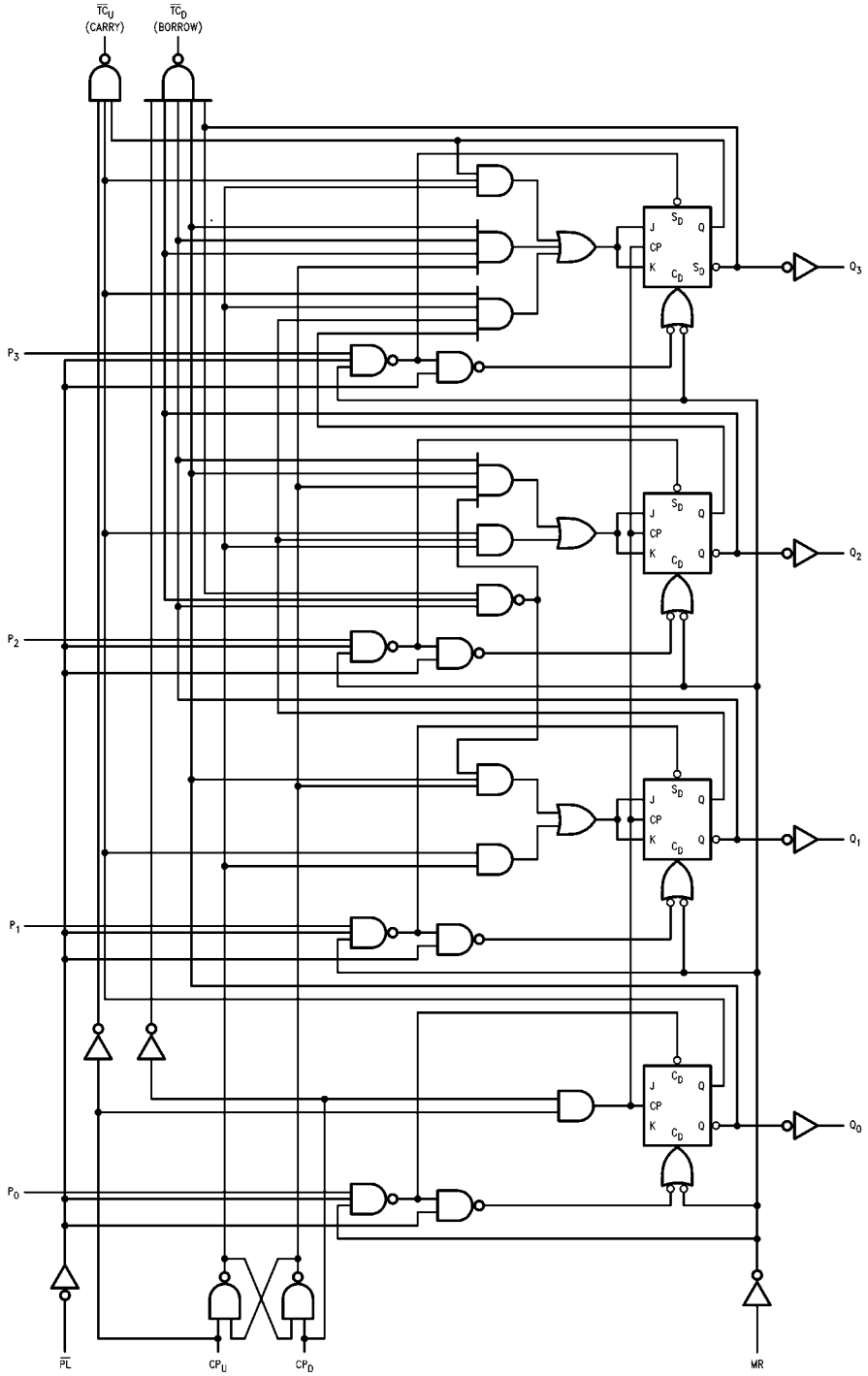
MR	$\overline{PL}$	CP_U	CP_D	Mode
H	X	X	X	Reset (Asyn.)
L	L	X	X	Preset (Asyn.)
L	H	H	H	No Change
L	H	⌐	H	Count Up
L	H	H	⌐	Count Down

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

State Diagram



Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V, Except CP_u, CP_D
					−1.8			V_{IN} = 0.5V, CP_u, CP_D
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCL}	Power Supply Current			38	55	mA	Max	V_O = LOW

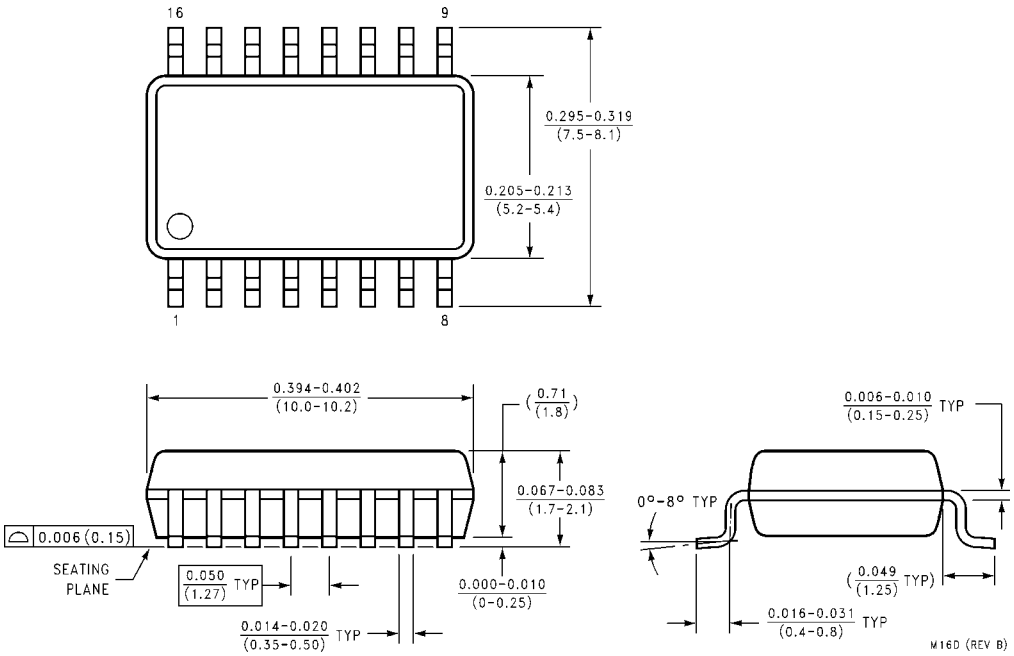
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	125		75		90		MHz
t_{PLH}	Propagation Delay CP_U or	4.0	7.0	9.0	4.0	10.5	4.0	10.0	ns
t_{PHL}	CP_D to $\overline{TC}_U$ or $\overline{TC}_D$	3.5	6.0	8.0	3.5	9.5	3.5	9.0	
t_{PLH}	Propagation Delay	4.0	6.5	8.5	4.0	10.0	4.0	9.5	ns
t_{PHL}	CP_U or CP_D to Q_n	5.5	9.5	12.5	5.5	14.0	5.5	13.5	
t_{PLH}	Propagation Delay	3.0	4.5	7.0	3.0	8.5	3.0	8.0	ns
t_{PHL}	P_n to Q_n	6.0	11.0	14.5	6.0	16.5	6.0	15.5	
t_{PLH}	Propagation Delay	5.0	8.5	11.0	5.0	13.5	5.0	12.0	ns
t_{PHL}	$\overline{PL}$ to Q_n	5.5	10.0	13.0	5.5	15.0	5.5	14.0	
t_{PHL}	Propagation Delay MR to Q_n	6.5	11.0	14.5	6.5	16.0	6.5	15.5	ns
t_{PLH}	Propagation Delay MR to $\overline{TC}_U$	6.0	10.5	13.5	6.0	15.0	6.0	14.5	
t_{PHL}	Propagation Delay MR to $\overline{TC}_D$	7.0	11.5	14.5	7.0	16.0	7.0	15.5	
t_{PLH}	Propagation Delay	7.0	12.0	15.5	7.0	18.5	7.0	16.5	ns
t_{PHL}	$\overline{PL}$ to $\overline{TC}_U$ or $\overline{TC}_D$	7.0	11.5	14.5	7.0	17.5	7.0	15.5	
t_{PLH}	Propagation Delay	7.0	11.5	14.5	7.0	16.5	7.0	15.5	ns
t_{PHL}	P_n to $\overline{TC}_U$ or $\overline{TC}_D$	6.5	11.0	14.0	6.5	16.5	6.5	15.0	

AC Operating Requirements

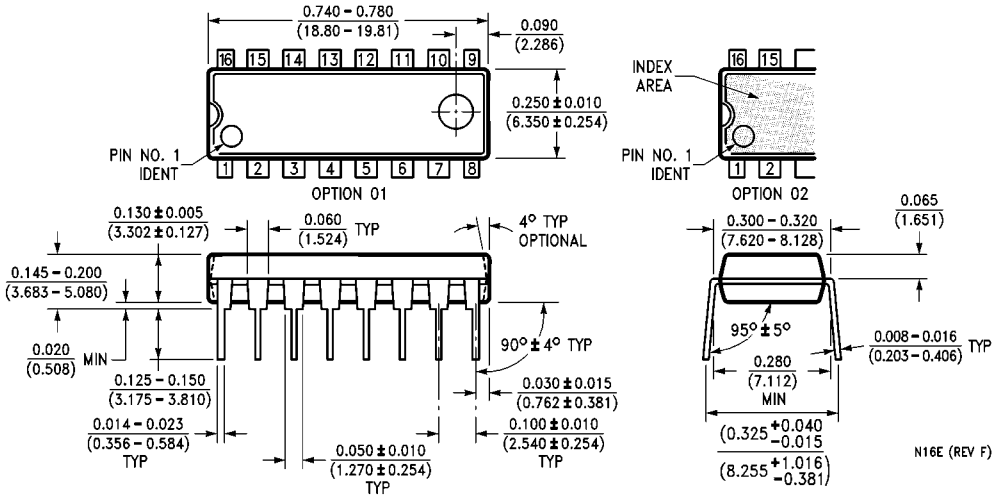
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$		$T_A = 0°C$ to $+70°C$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.5		6.0		5.0		ns
$t_S(L)$	P_n to $\overline{PL}$	4.5		6.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	P_n to $\overline{PL}$	2.0		2.0		2.0		
$t_W(L)$	$\overline{PL}$ Pulse Width, LOW	6.0		7.5		6.0		ns
$t_W(L)$	CP_U or CP_D Pulse Width, LOW	5.0		7.0		5.0		ns
$t_W(L)$	CP_U or CP_D Pulse Width, LOW (Change of Direction)	10.0		12.0		10.0		ns
$t_W(H)$	$\overline{MR}$ Pulse Width, HIGH	6.0		6.0		6.0		ns
t_{REC}	Recovery Time $\overline{PL}$ to CP_U or CP_D	6.0		8.0		6.0		ns
t_{REC}	Recovery Time MR to CP_U or CP_D	4.0		4.5		4.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F193
Up/Down Binary Counter with Separate Up/Down Clocks

General Description

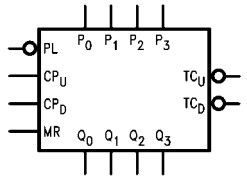
The 74F193 is an up/down modulo-16 binary counter. Separate Count Up and Count Down Clocks are used, and in either counting mode the circuits operate synchronously. The outputs change state synchronously with the LOW-to-HIGH transitions on the clock inputs. Separate Terminal Count Up and Terminal Count Down outputs are provided that are used as the clocks for subsequent stages without extra logic, thus simplifying multi-stage counter designs. Individual preset inputs allow the circuit to be used as a programmable counter. Both the Parallel Load ($\overline{PL}$) and the Master Reset (MR) inputs asynchronously override the clocks.

Ordering Code:

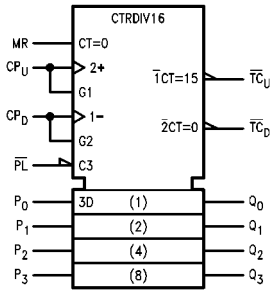
Order Number	Package Number	Package Description
74F193SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74F193SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F193PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

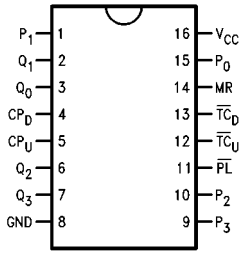
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
CP_U	Count Up Clock Input (Active Rising Edge)	1.0/3.0	20 μA/–1.8 mA
CP_D	Count Down Clock Input (Active Rising Edge)	1.0/3.0	20 μA/–1.8 mA
MR	Asynchronous Master Reset Input (Active HIGH)	1.0/1.0	20 μA/–0.6 mA
$\overline{PL}$	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
$\overline{TC}_D$	Terminal Count Down (Borrow) Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{TC}_U$	Terminal Count Up (Carry) Output (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The 74F193 is a 4-bit binary synchronous up/down (reversible) counter. It contains four edge-triggered flip-flops, with internal gating and steering logic to provide master reset, individual preset, count up and count down operations.

A LOW-to-HIGH transition on the CP input to each flip-flop causes the output to change state. Synchronous switching, as opposed to ripple counting, is achieved by driving the steering gates of all stages from a common Count Up line and a common Count Down line, thereby causing all state changes to be initiated simultaneously. A LOW-to-HIGH transition on the Count Up input will advance the count by one; a similar transition on the Count Down input will decrease the count by one. While counting with one clock input, the other should be held HIGH, as indicated in the Function Table.

The Terminal Count Up ($\overline{TC}_U$) and Terminal Count Down ($\overline{TC}_D$) outputs are normally HIGH. When the circuit has reached the maximum count state 15, the next HIGH-to-LOW transition of the Count Up Clock will cause $\overline{TC}_U$ to go LOW. $\overline{TC}_U$ will stay LOW until CP_U goes HIGH again, thus effectively repeating the Count Up Clock, but delayed by two gate delays. Similarly, the $\overline{TC}_D$ output will go LOW when the circuit is in the zero state and the Count Down Clock goes LOW. Since the $\overline{TC}$ outputs repeat the clock waveforms, they can be used as the clock input signals to the next higher order circuit in a multistage counter.

$$\overline{TC}_U = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet \overline{CP}_U$$

$$\overline{TC}_D = \overline{Q}_0 \bullet \overline{Q}_1 \bullet \overline{Q}_2 \bullet \overline{Q}_3 \bullet \overline{CP}_D$$

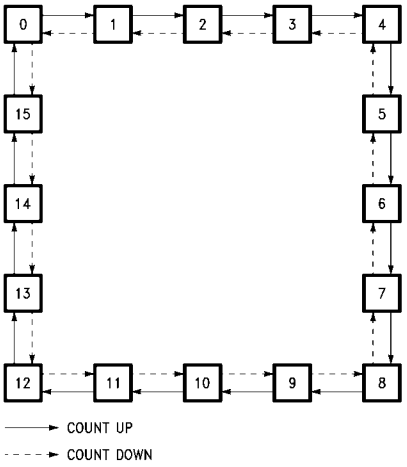
The 74F193 has an asynchronous parallel load capability permitting the counter to be preset. When the Parallel Load ($\overline{PL}$) and the Master Reset (MR) inputs are LOW, information present on the Parallel Data input (P_0–P_3) is loaded into the counter and appears on the outputs regardless of the conditions of the clock inputs. A HIGH signal on the Master Reset input will disable the preset gates, override both clock inputs, and latch each Q output in the LOW state. If one of the clock inputs is LOW during and after a reset or load operation, the next LOW-to-HIGH transition of that clock will be interpreted as a legitimate signal and will be counted.

Function Table

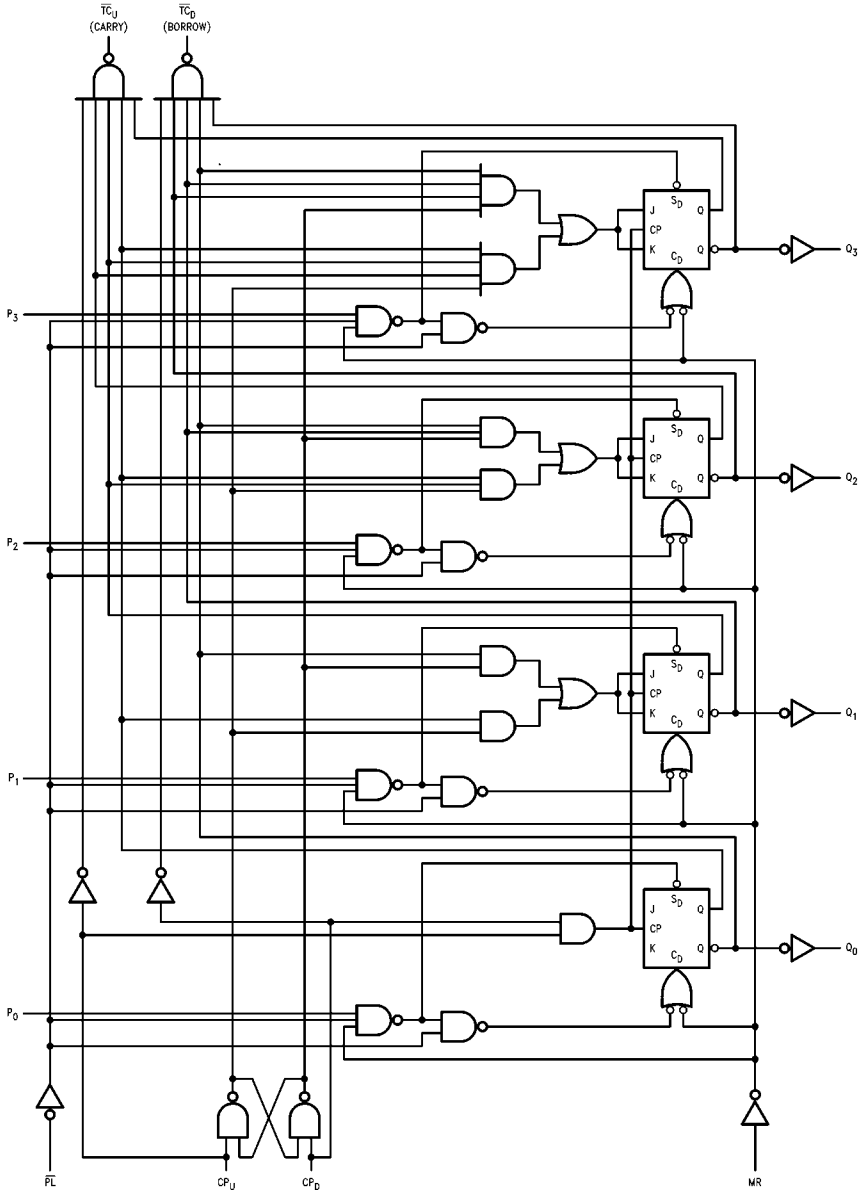
MR	$\overline{PL}$	CP_U	CP_D	Mode
H	X	X	X	Reset (Asyn.)
L	L	X	X	Preset (Asyn.)
L	H	H	H	No Change
L	H	⌐	H	Count Up
L	H	H	⌐	Count Down

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

State Diagram



Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0		Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100 7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6 −1.8	mA	Max	V_{IN} = 0.5V (MR, $\overline{PL}$, P_n) V_{IN} = 0.5V (CP_u, CP_D)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			38	55	mA	Max	

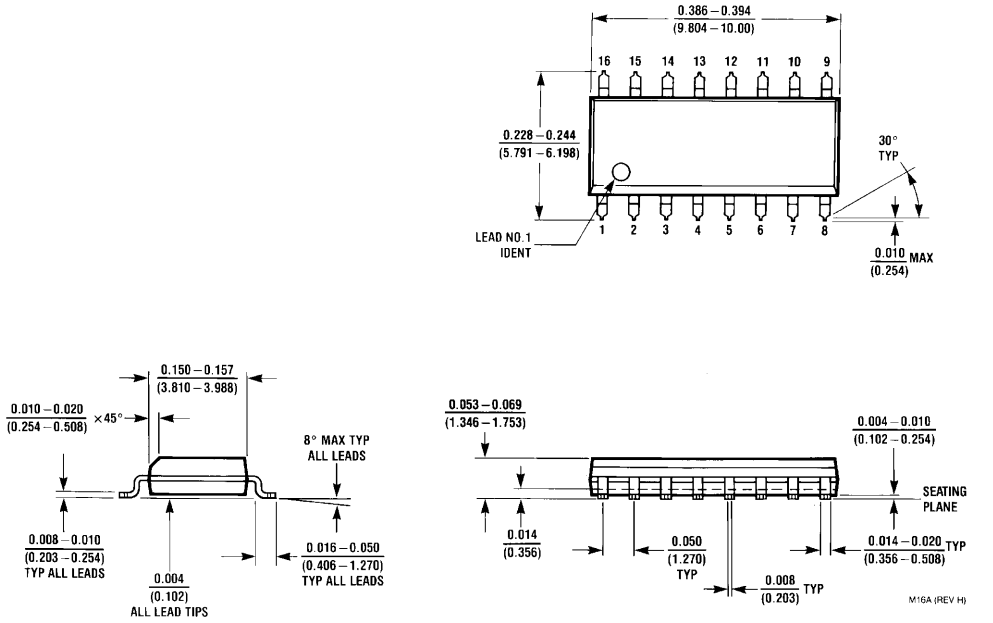
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Count Frequency	100	125		90		MHz
t_{PLH} t_{PHL}	Propagation Delay CP_U or CP_D to $\overline{TC}_U$ or $\overline{TC}_D$	4.0 3.5	7.0 6.0	9.0 8.0	4.0 3.5	10.0 9.0	ns
t_{PLH} t_{PHL}	Propagation Delay CP_U or CP_D to Q_n	4.0 5.5	6.5 9.5	8.5 12.5	4.0 5.5	9.5 13.5	ns
t_{PLH} t_{PHL}	Propagation Delay P_n to Q_n	3.0 6.0	4.5 11.0	7.0 14.5	3.0 6.0	8.0 15.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{PL}$ to Q_n	5.0 5.5	8.5 10.0	11.0 13.0	5.0 5.5	12.0 14.0	ns
t_{PHL}	Propagation Delay MR to Q_n	5.5	11.0	14.5	5.5	15.5	ns
t_{PLH}	Propagation Delay MR to $\overline{TC}_U$	6.0	10.5	13.5	6.0	14.5	
t_{PHL}	Propagation Delay MR to $\overline{TC}_D$	6.0	11.5	14.5	6.0	15.5	
t_{PLH} t_{PHL}	Propagation Delay $\overline{PL}$ to $\overline{TC}_U$ or $\overline{TC}_D$	7.0 7.0	12.0 11.5	15.5 14.5	7.0 7.0	16.5 15.5	ns
t_{PLH} t_{PHL}	Propagation Delay P_n to $\overline{TC}_U$ or $\overline{TC}_D$	7.0 6.5	11.5 11.0	14.5 14.0	7.0 6.5	15.5 15.0	ns

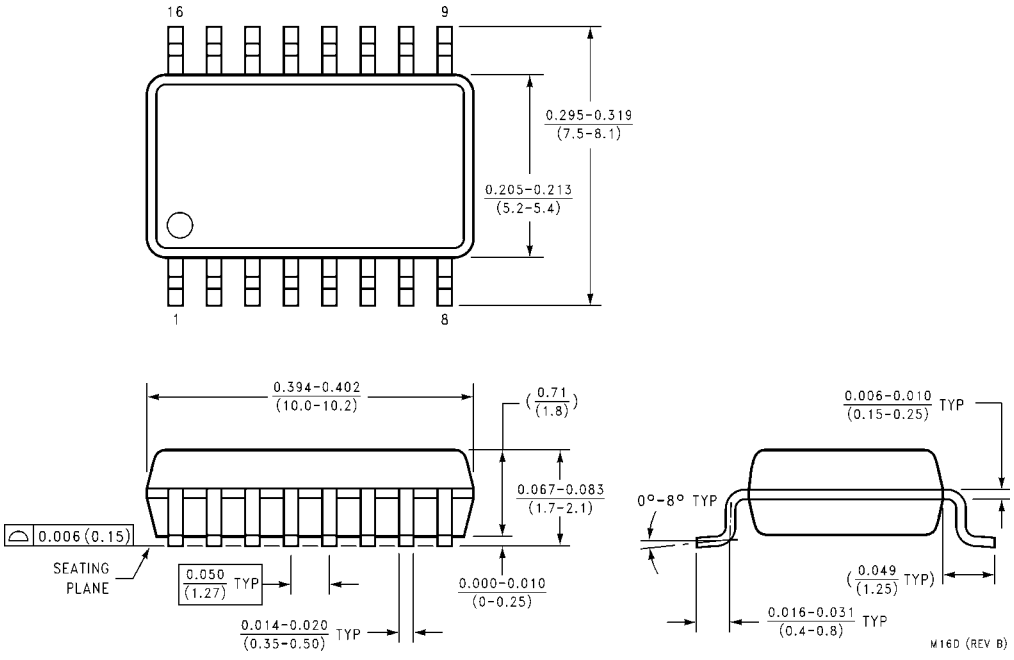
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW P_n to $\overline{PL}$	4.5 4.5		5.0 5.0		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW P_n to $\overline{PL}$	2.0 2.0		2.0 2.0		ns
$t_W(L)$	$\overline{PL}$ Pulse Width, LOW	6.0		6.0		ns
$t_W(L)$	CP_U or CP_D Pulse Width, LOW	5.0		5.0		ns
$t_W(L)$	CP_U or CP_D Pulse Width, LOW (Change of Direction)	10.0		10.0		ns
$t_W(H)$	MR Pulse Width, HIGH	6.0		6.0		ns
t_{REC}	Recovery Time $\overline{PL}$ to CP_U or CP_D	6.0		6.0		ns
t_{REC}	Recovery Time MR to CP_U or CP_D	4.0		4.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

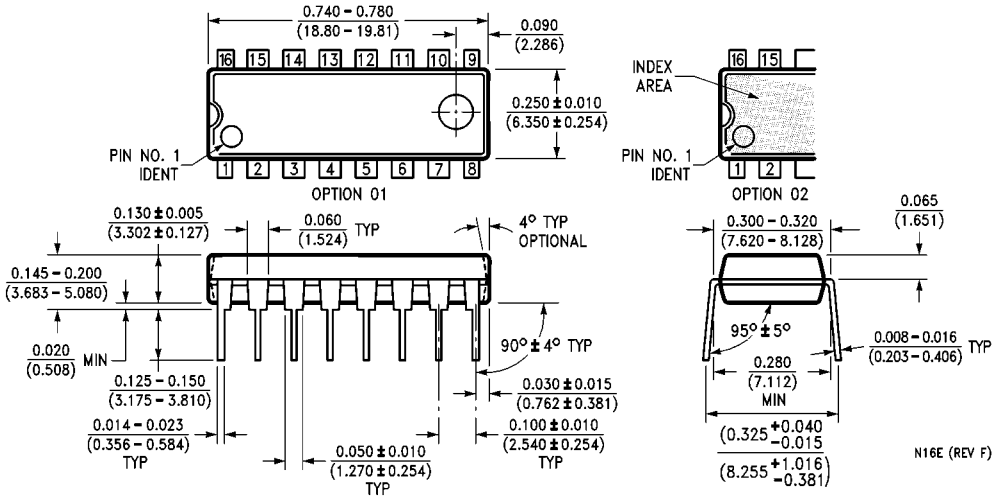


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F194
4-Bit Bidirectional Universal Shift Register

General Description

The 74F194 is a high-speed 4-bit bidirectional universal shift register. As a high-speed, multifunctional, sequential building block, it is useful in a wide variety of applications. It may be used in serial-serial, shift left, shift right, serial-parallel, parallel-serial, and parallel-parallel data register transfers. The 74F194 is similar in operation to the 74F195 universal shift register, with added features of shift left without external connections and hold (do nothing) modes of operation.

Features

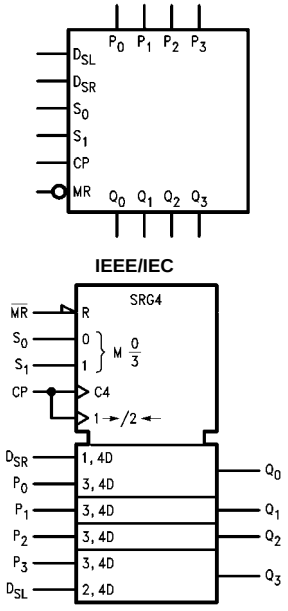
- Typical shift frequency of 150 MHz
- Asynchronous master reset
- Hold (do nothing) mode
- Fully synchronous serial or parallel data transfers

Ordering Code:

Order Number	Package Number	Package Description
74F194SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F194SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F194PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

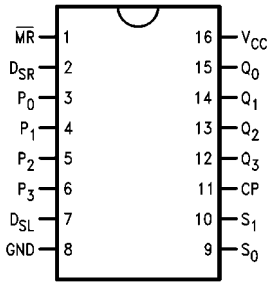
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0, S_1	Mode Control Inputs	1.0/1.0	20 µA/–0.6 mA
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
D_{SR}	Serial Data Input (Shift Right)	1.0/1.0	20 µA/–0.6 mA
D_{SL}	Serial Data Input (Shift Left)	1.0/1.0	20 µA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{MR}$	Asynchronous Master Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
Q_0–Q_3	Parallel Outputs	50/33.3	–1 mA/20 mA

Functional Description

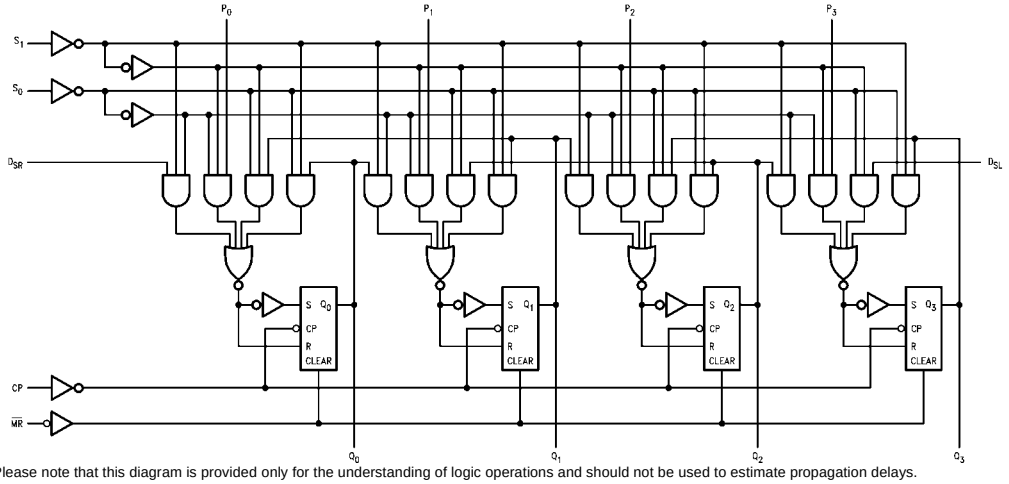
The 74F194 contains four edge-triggered D-type flip-flops and the necessary interstage logic to synchronously perform shift right, shift left, parallel load and hold operations. Signals applied to the Select (S_0, S_1) inputs determine the type of operation, as shown in the Mode Select Table. Signals on the Select, Parallel data (P_0–P_3) and Serial data (D_{SR}, D_{SL}) inputs can change when the clock is in either state, provided only that the recommended setup and hold times, with respect to the clock rising edge, are observed. A LOW signal on Master Reset ($\overline{MR}$) overrides all other inputs and forces the outputs LOW.

Mode Select Table

Operating Mode	Inputs						Outputs			
	$\overline{MR}$	S_1	S_0	D_{SR}	D_{SL}	P_n	Q_0	Q_1	Q_2	Q_3
Reset	L	X	X	X	X	X	L	L	L	L
Hold	H	l	l	X	X	X	q_0	q_1	q_2	q_3
Shift Left	H	h	l	X	l	X	q_1	q_2	q_3	L
	H	h	l	X	h	X	q_1	q_2	q_3	H
Shift Right	H	l	h	l	X	X	L	q_0	q_1	q_2
	H	l	h	h	X	X	H	q_0	q_1	q_2
Parallel Load	H	h	h	X	X	p_n	p_0	p_1	p_2	p_3

H (h) = HIGH Voltage Level
L (l) = LOW Voltage Level
p_n (q_n) = Lower case letters indicate the state of the referenced input (or output) one setup time prior to the LOW-to-HIGH clock transition.
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5			I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	μA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	μA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			33	46	mA	Max	

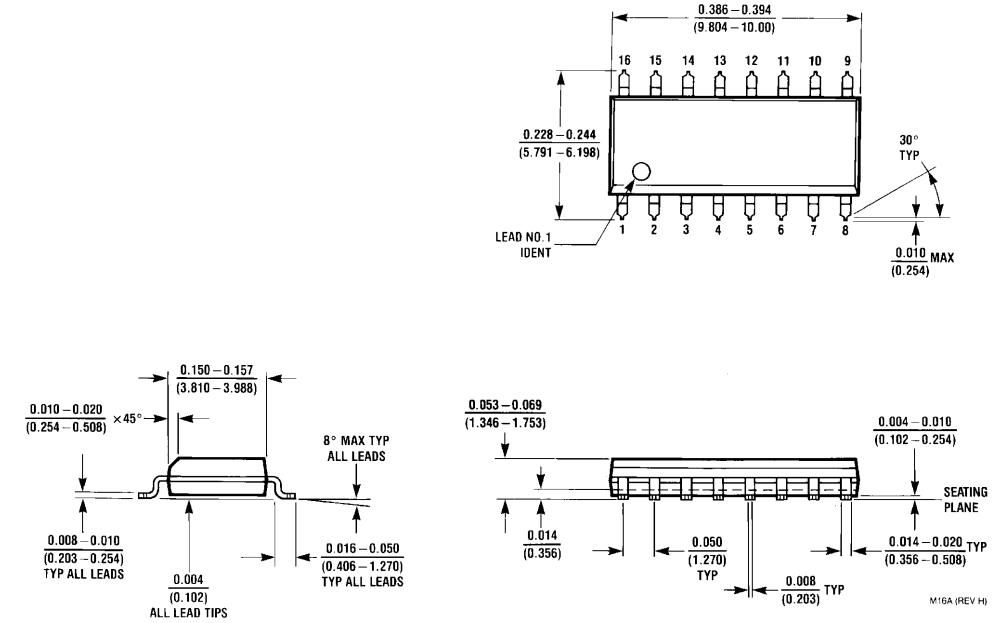
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Shift Frequency	105	150		90		90		MHz
t_{PLH}	Propagation Delay	3.5	5.2	7.0	3.0	8.5	3.5	8.0	ns
t_{PHL}	CP to Q_n	3.5	5.5	7.0	3.0	8.5	3.5	8.0	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_n	4.5	8.6	12.0	4.5	14.5	4.5	14.0	ns

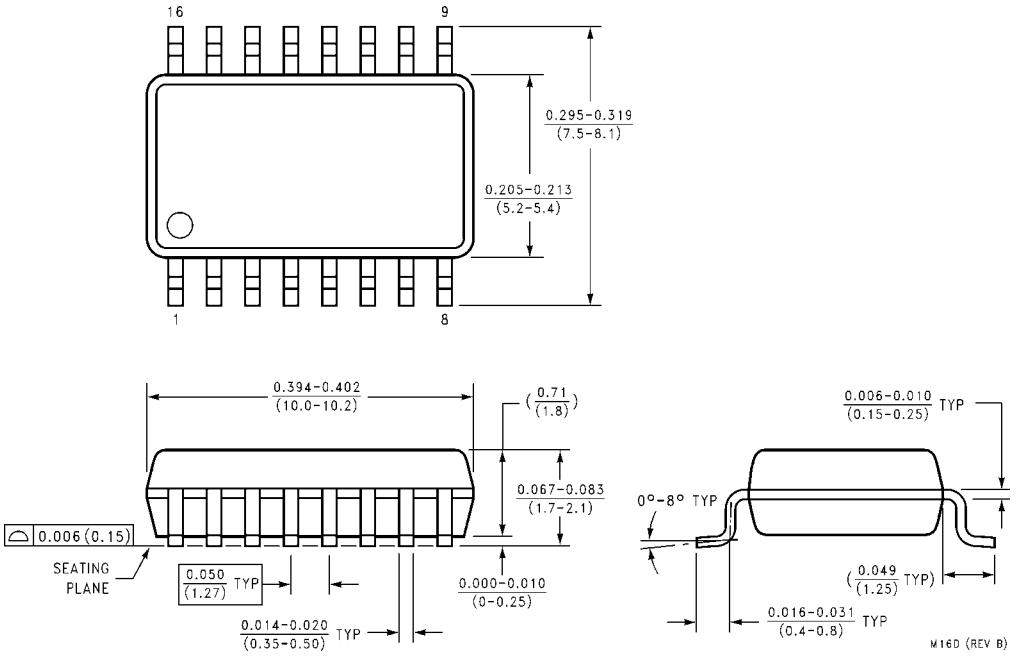
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		6.0		4.0		ns
$t_S(L)$	P_n or D_{SR} or D_{SL} to CP	4.0		4.0		4.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.5		1.0		
$t_H(L)$	P_n or D_{SR} or D_{SL} to CP	0		1.0		1.0		
$t_S(H)$	Setup Time, HIGH or LOW	10.0		10.5		11.0		ns
$t_S(L)$	S_n to CP	8.0		8.0		8.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	S_n to CP	0		0		0		
$t_W(H)$	CP Pulse Width, HIGH	5.0		5.5		5.5		ns
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	5.0		5.0		5.0		ns
t_{REC}	Recovery Time $\overline{MR}$ to CP	9.0		9.0		11.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

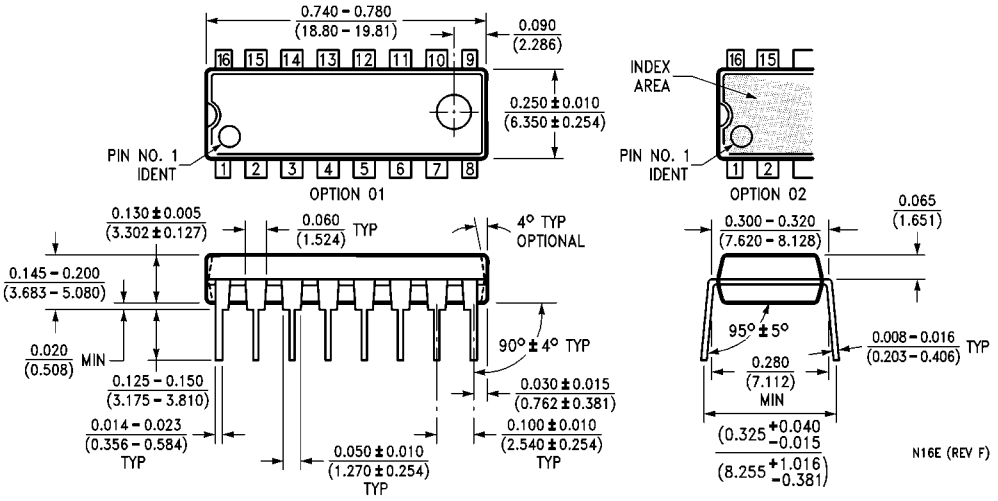


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F20
Dual 4-Input NAND Gate

General Description

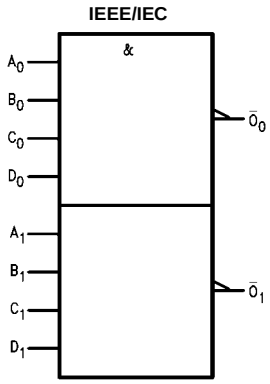
This device contains two independent gates, each of which performs the logic NAND function.

Ordering Code:

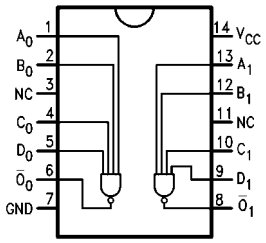
Order Number	Package Number	Package Description
74F20SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F20SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F20PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n, C_n, D_n	Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

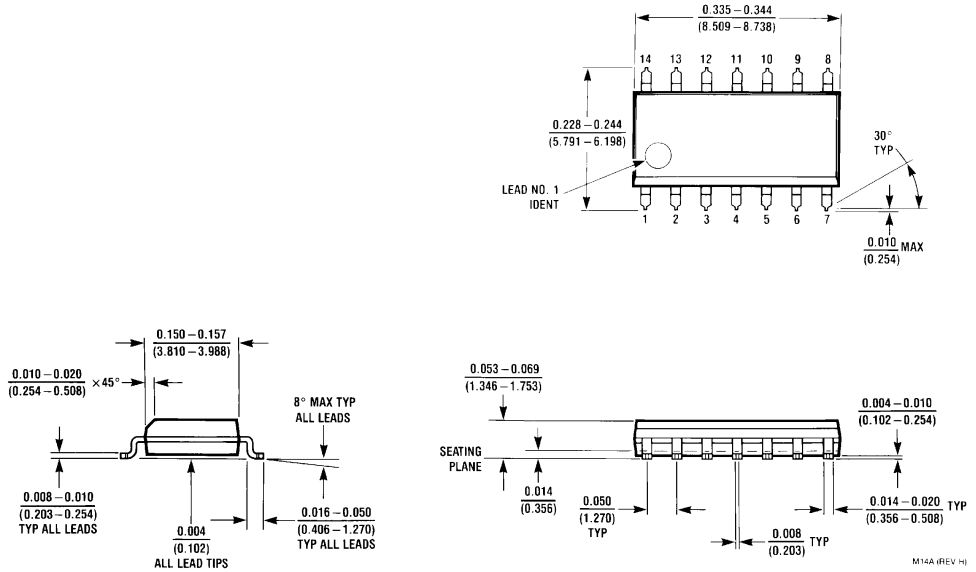
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			0.9	1.4	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			3.4	5.1	mA	Max	V_O = LOW

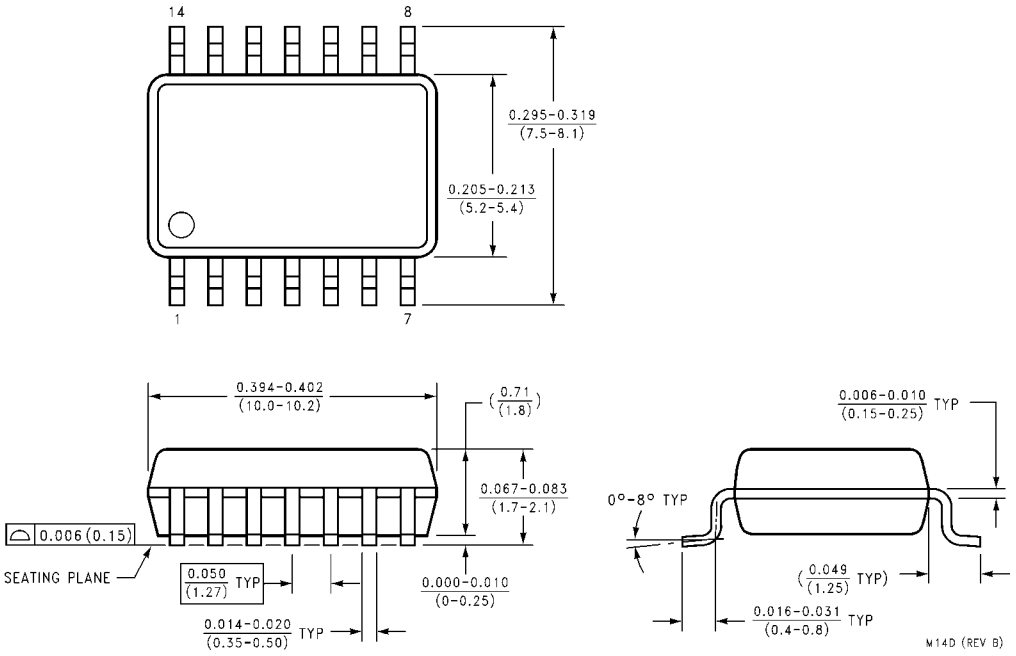
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55° to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	ns
t_{PHL}	A_n, B_n, C_n, D_n to $\overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3	

Physical Dimensions inches (millimeters) unless otherwise noted

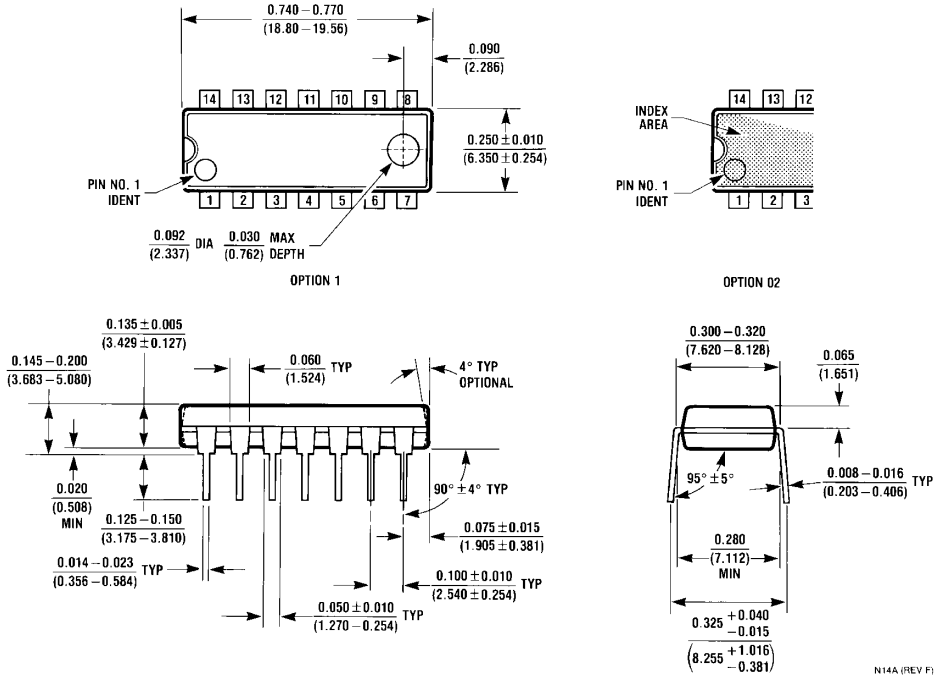


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

June 1988
Revised July 1999

74F219
64-Bit Random Access Memory with 3-STATE Outputs

General Description

The 74F219 is a high-speed 64-bit RAM organized as a 16-word by 4-bit array. Address inputs are buffered to minimize loading and are fully decoded on-chip. The outputs are 3-STATE and are in the high-impedance state whenever the Chip Select ($\overline{CS}$) input is HIGH. The outputs are active only in the Read mode. This device is similar to the 74F189 but features non-inverting, rather than inverting, data outputs.

Features

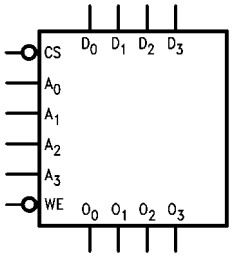
- 3-STATE outputs for data bus applications
- Buffered inputs minimize loading
- Address decoding on-chip
- Diode clamped inputs minimize ringing
- Available in SOIC (300 mil only)

Ordering Code:

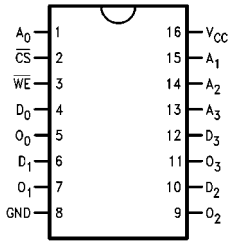
Order Number	Package Number	Package Description
74F219SC	M16B	16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F219SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F219PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

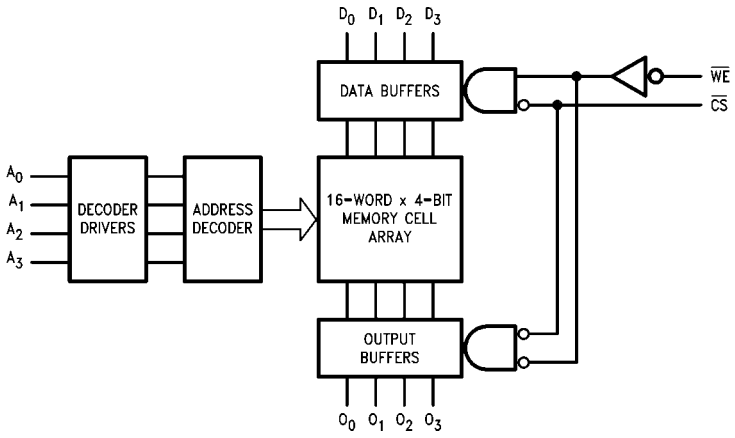
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	Address Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/2.0	20 μA/–1.2 mA
$\overline{WE}$	Write Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
D_0–D_3	Data Inputs	1.0/1.0	20 μA/–0.6 mA
O_0–O_3	3-STATE Data Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Function Table

Inputs		Operation	Condition of Outputs
$\overline{CS}$	$\overline{WE}$		
L	L	Write	High Impedance
L	H	Read	True Stored Data
H	X	Inhibit	High Impedance

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (A_n, $\overline{WE}$, D_n)
					−1.2			V_{IN} = 0.5V ($\overline{CS}$)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CC}	Power Supply Current			37	55	mA	Max	

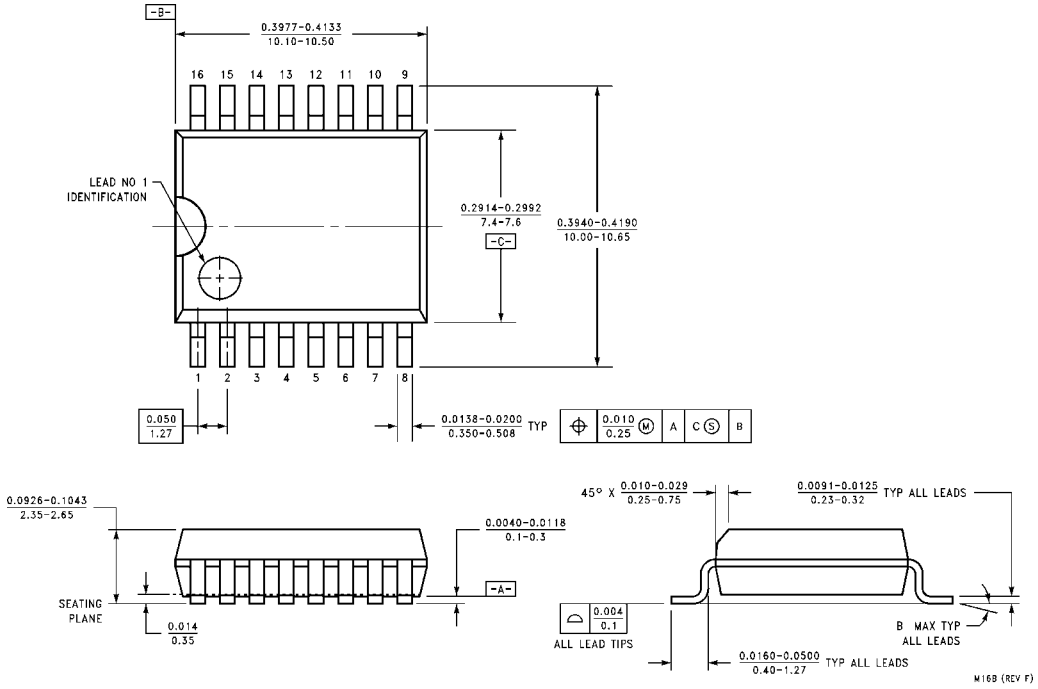
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Access Time, HIGH or LOW	10.0	18.5	26.0	9.0	32.0	10.0	27.0	ns
t_{PHL}	A_n to O_n	8.0	13.5	19.0	8.0	23.0	8.0	20.0	
t_{PZH}	Access Time, HIGH or LOW	3.5	6.0	8.5	3.5	10.5	3.5	9.5	ns
t_{PZL}	$\overline{CS}$ to O_n	5.0	9.0	13.0	5.0	15.0	5.0	14.0	
t_{PHZ}	Disable Time, HIGH or LOW	2.0	4.0	6.0	2.0	8.0	2.0	7.0	
t_{PLZ}	$\overline{CS}$ to O_n	3.0	5.5	8.0	2.5	10.0	3.0	9.0	
t_{PZH}	Write Recovery Time	6.5	20.0	28.0	6.5	37.5	6.5	29.0	ns
t_{PZL}	HIGH or LOW, $\overline{WE}$ to O_n	6.5	11.0	15.5	6.5	17.5	6.5	16.5	
t_{PHZ}	Disable Time, HIGH or LOW	4.0	7.0	10.0	3.5	12.0	4.0	11.0	
t_{PLZ}	$\overline{WE}$ to O_n	5.0	9.0	13.0	5.0	15.0	5.0	14.0	

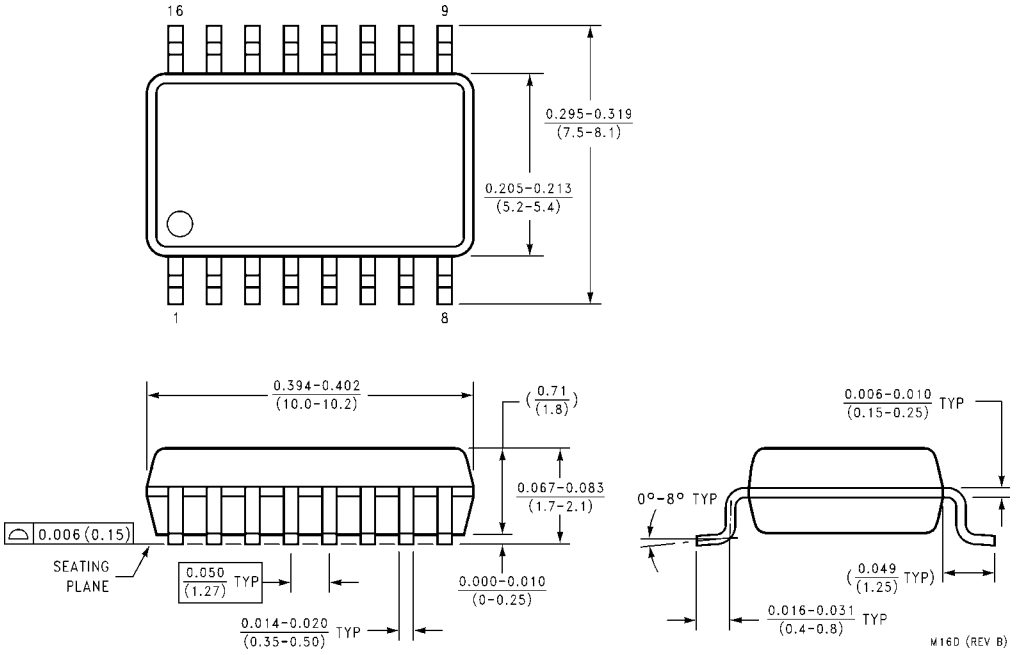
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	0		0		0		ns
$t_S(L)$	A_n to $\overline{WE}$	0		0		0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	A_n to $\overline{WE}$	2.0		2.0		2.0		
$t_S(H)$	Setup Time, HIGH or LOW	10.0		11.0		10.0		ns
$t_S(L)$	D_n to $\overline{WE}$	10.0		11.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		2.0		0		
$t_H(L)$	D_n to $\overline{WE}$	0		2.0		0		
$t_S(L)$	Setup Time, LOW $\overline{CS}$ to $\overline{WE}$	0		0		0		ns
$t_H(L)$	Hold Time, LOW $\overline{CS}$ to $\overline{WE}$	6.0		7.5		6.0		
$t_W(L)$	$\overline{WE}$ Pulse Width, LOW	6.0		15.0		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

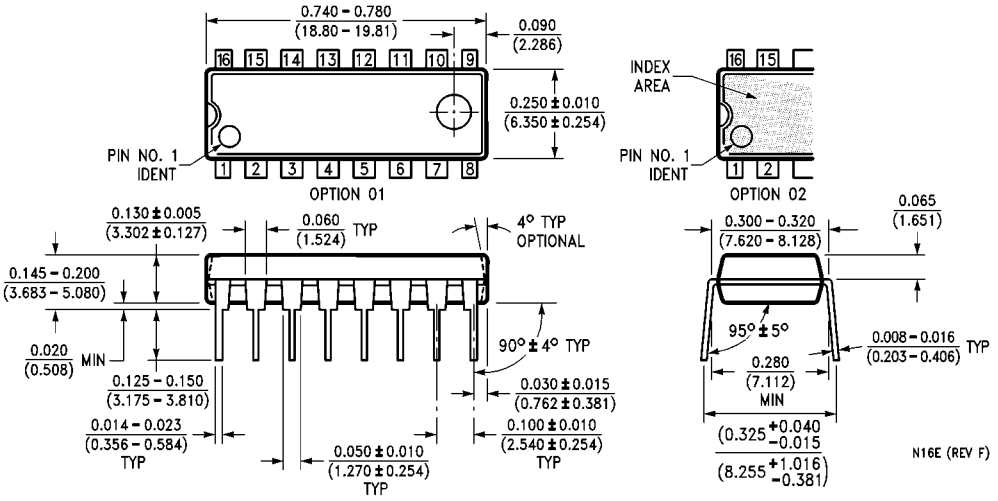


16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M16B



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

January 1995
Revised May 1999

74F2240
Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The 74F2240 is an inverting octal buffer and line driver designed to drive capacitive inputs of MOS memory devices, address and clock lines or act as a low undershoot general purpose bus driver.

The 25Ω series resistor in the outputs reduces undershoot and ringing and eliminates the need for external resistors.

Features

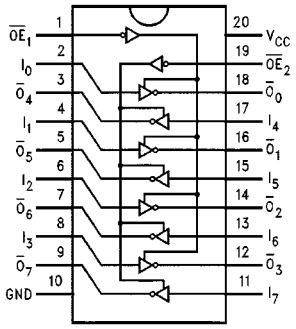
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 12 mA and source 15 mA
- 25Ω series resistors in outputs eliminate the need for external resistors
- Designed to drive the capacitive inputs of MOS devices
- Guaranteed 4000V minimum ESD protection

Ordering Code:

Order Number	Package Number	Package Description
74F2240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F2240QC	V20A	20-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.350 Square

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Truth Table

$\overline{OE}_1$	D_{1n}	O_{1n}	$\overline{OE}_2$	D_{2n}	O_{2n}
H	X	Z	H	X	Z
L	H	L	L	H	L
L	L	H	L	L	H

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Input (Active LOW)	1.0/1.667	20 μA/–1 mA
I_0 - I_7	Inputs	1.0/1.667	20 μA/–1 mA
$\overline{O}_0$ - $\overline{O}_7$	Outputs	750/20	–15 mA/12 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to + 150°C
Ambient Temperature under Bias	−55° to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
In HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to 70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

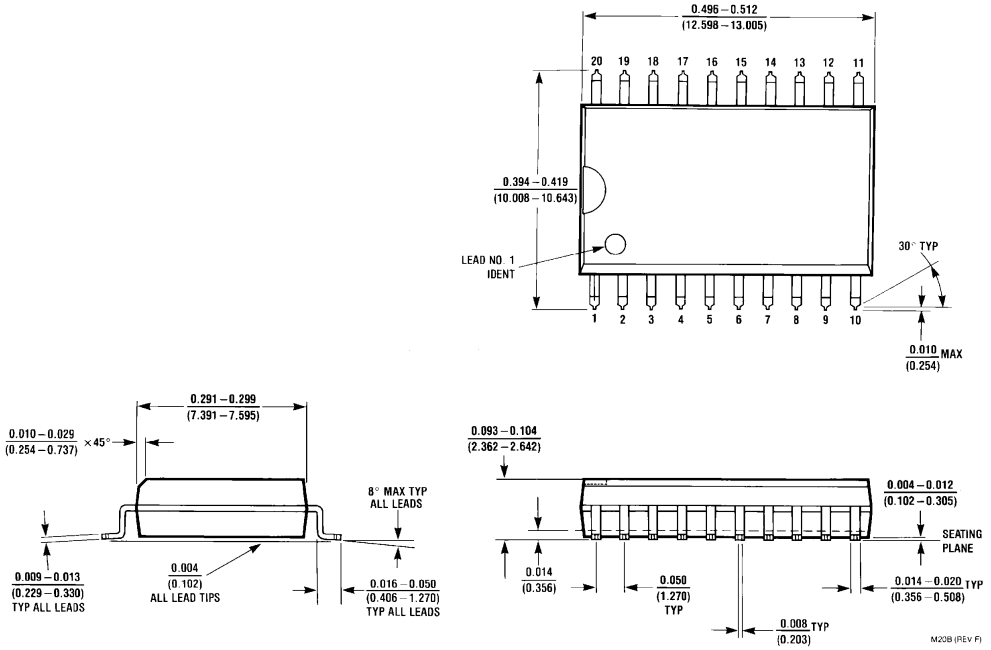
DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
	Voltage 10% V_{CC}	2.0					I_{OH} = −15 mA
V_{OL}	Output LOW Voltage 10% V_{CC}			0.75	V	Min	I_{OL} = 12 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−1.0	mA	Max	V_{IN} = 0.5V ($\overline{OE_1}$, $\overline{OE_2}$, D_n)
I_{OZH}	Output Leakage Current			50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		16	29	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		47	75	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		45	63	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

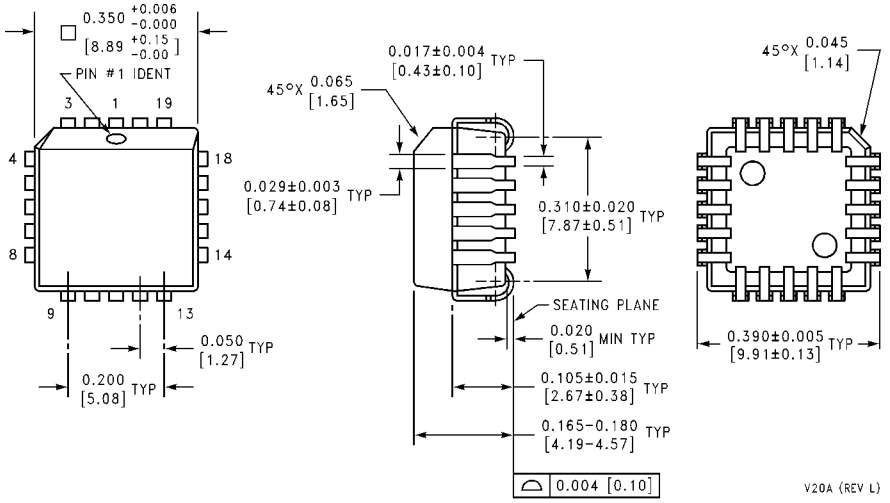
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	4.9	7.5	3.0	7.5	ns
t_{PHL}	Data to Output	2.0	3.7	6.0	2.0	6.0	
t_{PZH}	Output Enable Time	2.0	3.9	6.5	2.0	7.0	ns
t_{PZL}		4.0	6.7	9.5	4.0	10.0	
t_{PHZ}	Output Disable Time	2.0	4.1	6.5	2.0	7.0	ns
t_{PLZ}		2.0	4.9	8.5	2.0	9.5	

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.350 Square
Package Number V20A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1988
Revised August 1999

74F2243
Quad Bus Transceiver with 25Ω Series Resistors in the Outputs

General Description

The 74F2243 is a quad bus transmitter/receiver which can be used for 4-line asynchronous 2-way data communications between data busses. It is designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers, and bus-oriented transmitters/receivers.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

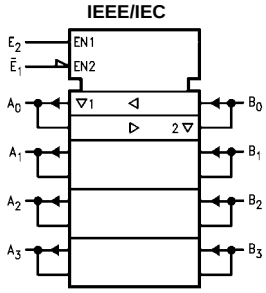
- 25Ω series resistors in outputs eliminate the need for external resistors
- 2-Way asynchronous data bus communication
- 3-STATE outputs
- 12 mA source current
- Designed to drive the capacitive inputs of MOS devices

Ordering Code:

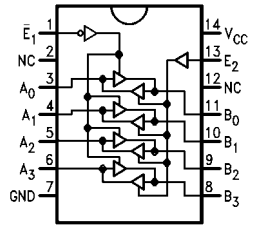
Order Number	Package Number	Package Description
74F2243SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Truth Table

Inputs		Inputs/Outputs	
$\bar{E}_1$	E_2	A_n	B_n
L	L	Input	B = A
L	H	N/A	N/A
H	L	Z	Z
H	H	A = B	Input

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
N/A = Not Allowed

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\bar{E}_1$	Enable Input (Active LOW)	1.0/1.67	20 μA/–1 mA
E_2	Enable Input (Active HIGH)	1.0/1.67	20 μA/–1 mA
A_n, B_n	Inputs	3.5/2.67	70 μA/–1.6 mA
	Outputs	750/20	–15 mA/12 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

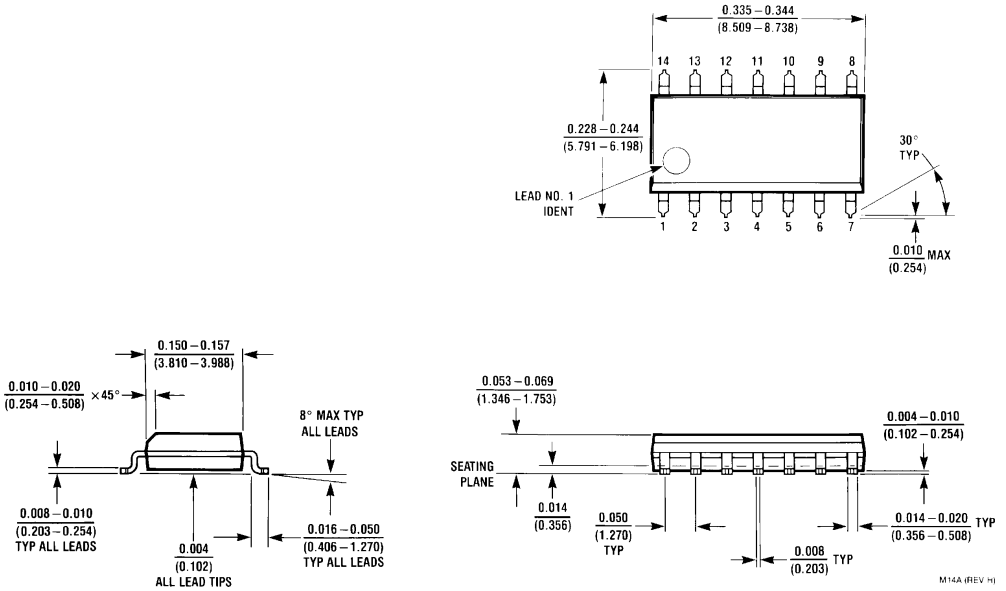
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
	Voltage	10% V_{CC}	2.0					I_{OH} = −15 mA (A_n, B_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n)
V_{OL}	Output LOW				0.50	V	Min	I_{OL} = 1 mA (A_n, B_n)
	Voltage				0.75			I_{OL} = 12 mA (A_n, B_n)
I_{IH}	Input HIGH Current				20	µA	Max	V_{IN} = 2.7V ($\overline{E}_1$, $\overline{E}_2$)
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	Max	V_{IN} = 7.0V ($\overline{E}_1$, E_2)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)				1.0	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current				−1.0	mA	Max	V_{IN} = 0.5V ($\overline{E}_1$, E_2)
$I_{IH} + I_{OZH}$	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current				−1.6	mA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current			64	80	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			64	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			71	90	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5		7.0	1.5	7.0	ns
t_{PHL}	A_n to B_n, B_n to A_n	2.5		8.0	2.0	8.0	
t_{PZH}	Output Enable Time	1.5		9.0	1.0	9.5	ns
t_{PZL}	$\overline{E}_1$ to B_n, E_2 to A_n	2.5		11.5	2.5	12.0	
t_{PHZ}	Output Disable Time	1.5		9.0	1.0	9.5	
t_{PLZ}	$\overline{E}_1$ to B_n, E_2 to A_n	1.5		8.5	1.5	9.5	

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1988
Revised March 1999

74F2244
Octal Buffer/Line Driver with 25Ω Series Resistors in Outputs

General Description

The F2244 is an octal buffer/line driver designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers and bus-oriented transmitters/receivers.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

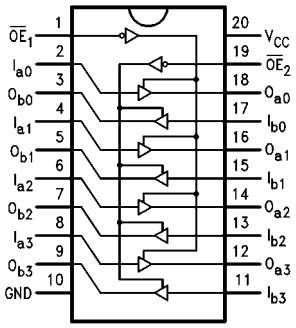
- 3-STATE outputs drive bus lines or buffer memory address registers
- 12 mA source current
- 25Ω series resistors in outputs eliminate the need for external resistors.
- Designed to drive the capacitive inputs of MOS devices
- Guaranteed 4000V minimum ESD protection

Ordering Code:

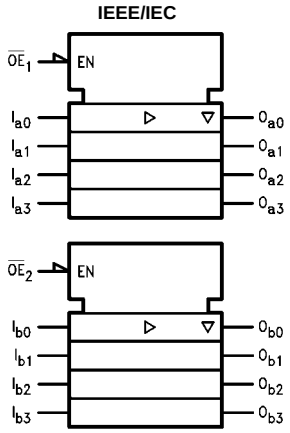
Order Number	Package Number	Package Description
74F2244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F2244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F2244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Input (Active LOW)	1.0/1.667	20 μA/–1 mA
OE_2	3-STATE Output Enable Input (Active HIGH)	1.0/1.667	20 μA/–1 mA
I_{an}, I_{bn}	Inputs	1.0/2.667 (Note 1)	20 μA/–1.6 mA
O_{an},O_{bn}	Outputs	750/20	–15 mA/12 mA

Note 1: Worst-case F2244 disabled

Truth Table

$\overline{OE}_1$	I_{an}	O_{an}	$\overline{OE}_2$	I_{bn}	O_{bn}
H	X	Z	H	X	Z
L	H	H	L	H	H
L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

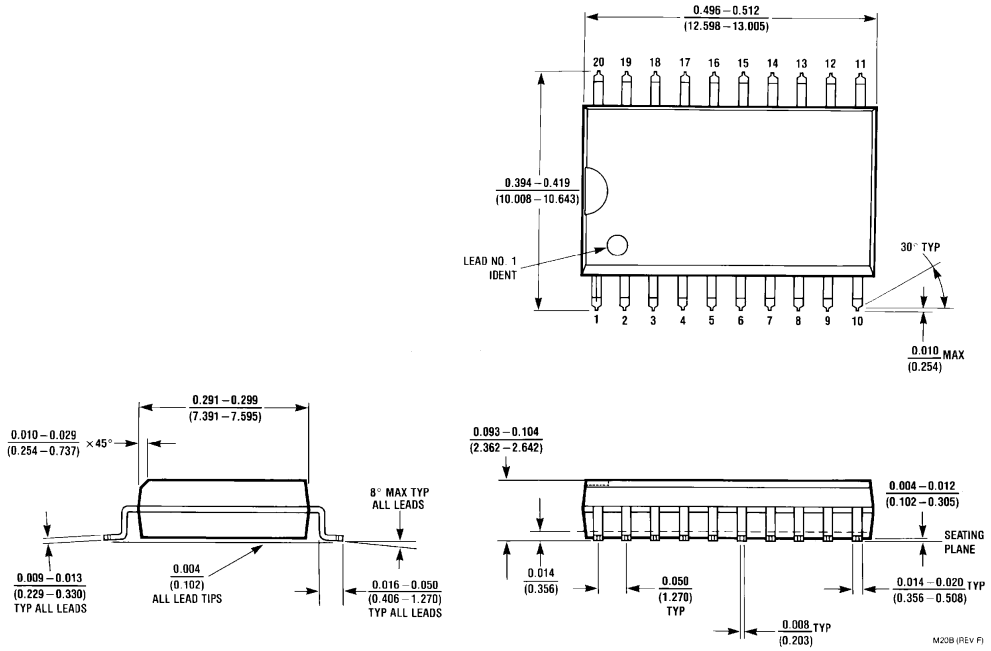
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		10% V_{CC}	2.0					I_{OH} = −15 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage				0.50	V	Min	I_{OL} = 1 mA
					0.75			I_{OL} = 12 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−1.0	mA	Max	V_{IN} = 0.5V ($\overline{OE}_1$, $\overline{OE}_2$, OE_2)
					−1.6			V_{IN} = 0.5V (I_n)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			40	60	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			60	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			60	90	mA	Max	V_O = HIGH Z

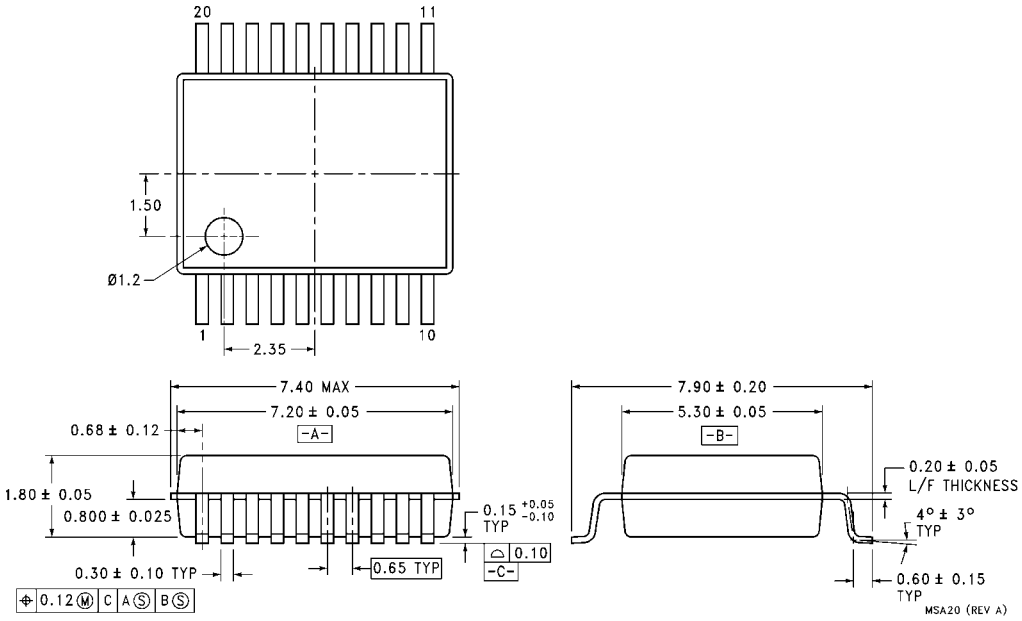
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5		7.0	2.0	6.5	1.5	7.0	ns
t_{PHL}	Data to Output	2.5		8.0	2.0	7.0	2.0	8.0	
t_{PZH}	Output Enable Time	1.5		9.0	2.0	7.0	1.0	9.5	
t_{PZL}		2.5		11.5	2.0	8.5	2.5	12.0	ns
t_{PHZ}	Output Disable Time	1.5		9.0	2.0	7.0	1.0	9.5	
t_{PLZ}		1.5		8.5	2.0	7.5	1.5	9.5	

Physical Dimensions inches (millimeters) unless otherwise noted

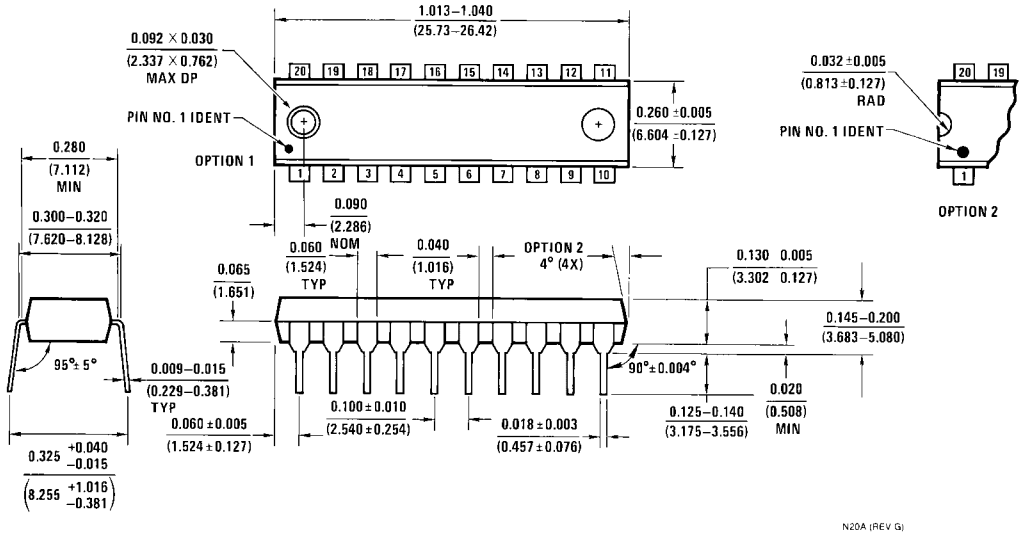


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F240 • 74F241 • 74F244
Octal Buffers/Line Drivers with 3-STATE Outputs

General Description

The 74F240, 74F241 and 74F244 are octal buffers and line drivers designed to be employed as memory and address drivers, clock drivers and bus-oriented transmitters/receivers which provide improved PC and board density.

Features

- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 64 mA (48 mA mil)
- 12 mA source current
- Input clamp diodes limit high-speed termination effects

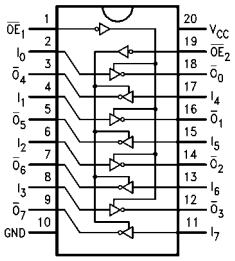
Ordering Code:

Order Code	Package Number	Package Description
74F240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F240PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F241SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F241SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F241PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

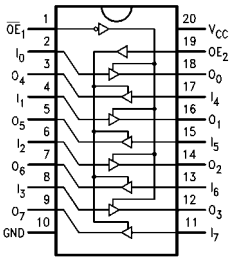
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

74F240



74F241



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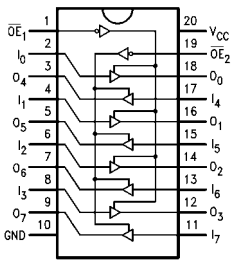
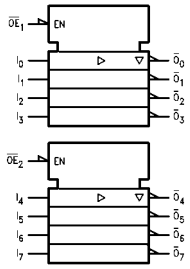
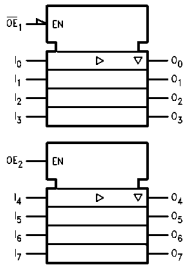


Logic Symbols

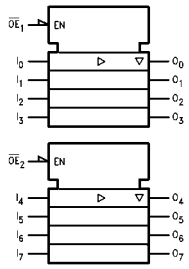
IEEE/IEC
74F240



IEEE/IEC
74F241



IEEE/IEC
74F244



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Input (Active LOW)	1.0/1.667	20 µA/–1 mA
OE_2	3-STATE Output Enable Input (Active HIGH)	1.0/1.667	20 µA/–1 mA
I_0–I_7	Inputs (74F240)	1.0/1.667 (Note 1)	20 µA/–1 mA
I_0–I_7	Inputs (74F241, 74F244)	1.0/2.667 (Note 1)	20 µA/–1.6 mA
$\overline{O}_0$–$\overline{O}_7$, O_0–O_7	Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Note 1: Worst-case 74F240 enabled; 74F241, 74F244 disabled

Truth Tables

74F240

$\overline{OE}_1$	D_{1n}	O_{1n}	$\overline{OE}_2$	D_{2n}	O_{2n}
H	X	Z	H	X	Z
L	H	L	L	H	L
L	L	H	L	L	H

74F241

$\overline{OE}_1$	D_{1n}	O_{1n}	OE_2	D_{2n}	O_{2n}
H	X	Z	L	X	Z
L	H	H	H	H	H
L	L	L	H	L	L

74F244

$\overline{OE}_1$	D_{1n}	O_{1n}	$\overline{OE}_2$	D_{2n}	O_{2n}
H	X	Z	H	X	Z
L	H	H	L	H	H
L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

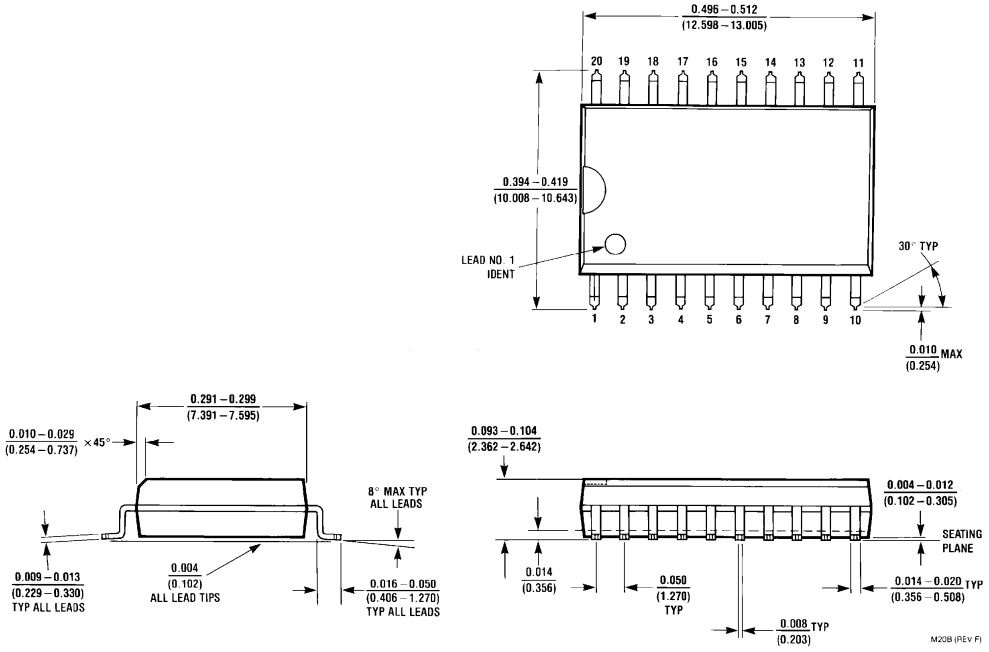
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		10% V_{CC}	2.0					I_{OH} = −15 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.0	mA	Max	V_{IN} = 0.5V ($\overline{OE}_1$, $\overline{OE}_2$, OE_2, D_n 74F240))
					−1.6			V_{IN} = 0.5V (D_n (74F241, 74F244))
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current (74F240)			19	29	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F240)			50	75	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F240)			42	63	mA	Max	V_O = HIGH Z
I_{CCH}	Power Supply Current (74F241, 74F244)			40	60	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F241, 74F244)			60	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F241, 74F244)			60	90	mA	Max	V_O = HIGH Z

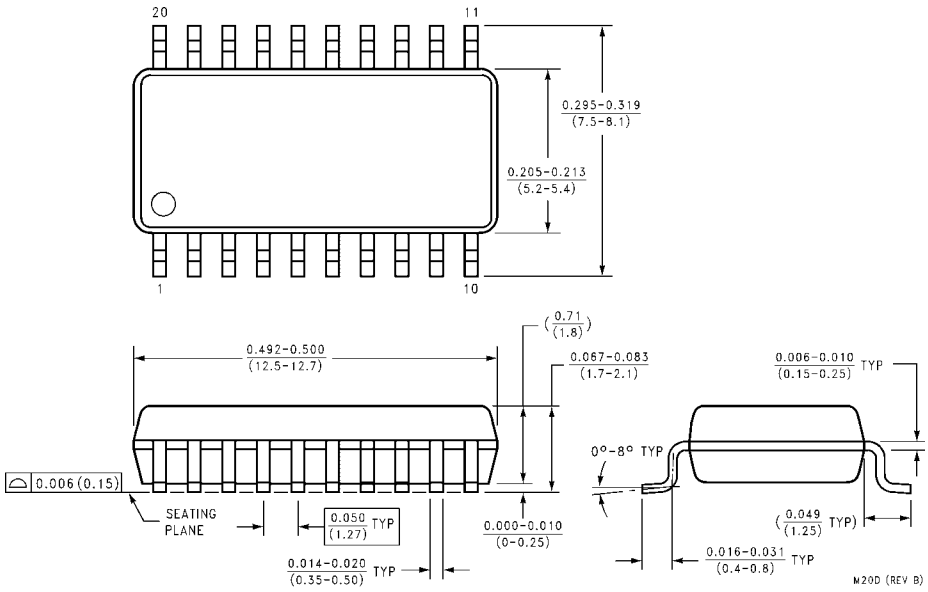
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	5.1	7.0	3.0	9.0	3.0	8.0	ns
t_{PHL}	Data to Output (74F240)	2.0	3.5	4.7	2.0	6.0	2.0	5.7	
t_{PZH}	Output Enable Time (74F240)	2.0	3.5	4.7	2.0	6.5	2.0	5.7	ns
t_{PZL}		4.0	6.9	9.0	4.0	10.5	4.0	10.0	
t_{PHZ}	Output Disable Time (74F240)	2.0	4.0	5.3	2.0	6.5	2.0	6.3	
t_{PLZ}		2.0	6.0	8.0	2.0	12.5	2.0	9.5	
t_{PLH}	Propagation Delay	2.5	4.0	5.2	2.0	6.5	2.5	6.2	ns
t_{PHL}	Data to Output (74F241, 74F244)	2.5	4.0	5.2	2.0	7.0	2.5	6.5	
t_{PZH}	Output Enable Time	2.0	4.3	5.7	2.0	7.0	2.0	6.7	ns
t_{PZL}	(74F241, 74F244)	2.0	5.4	7.0	2.0	8.5	2.0	8.0	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	2.0	7.0	2.0	7.0	
t_{PLZ}	(74F241, 74F244)	2.0	4.5	6.0	2.0	7.5	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted

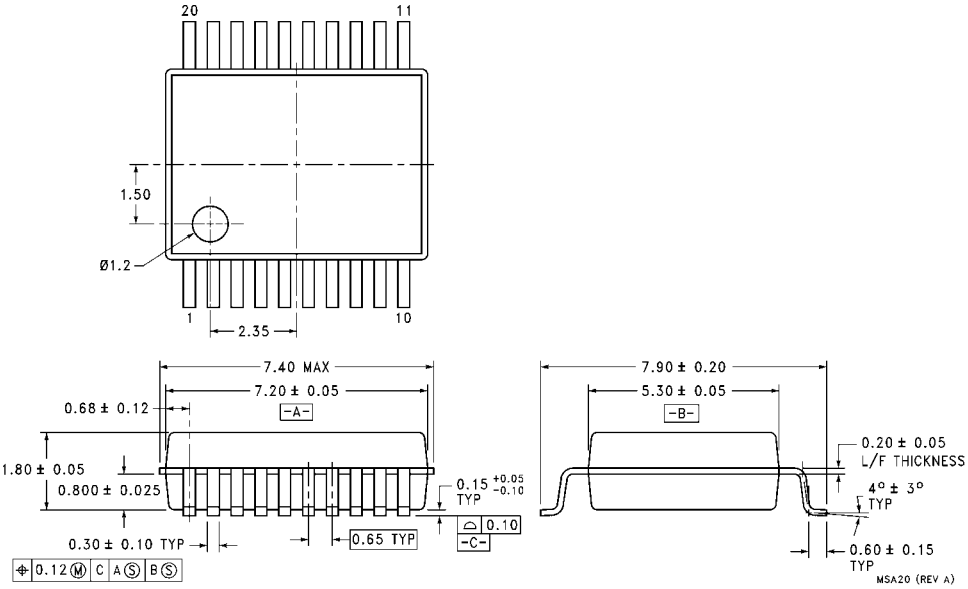


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



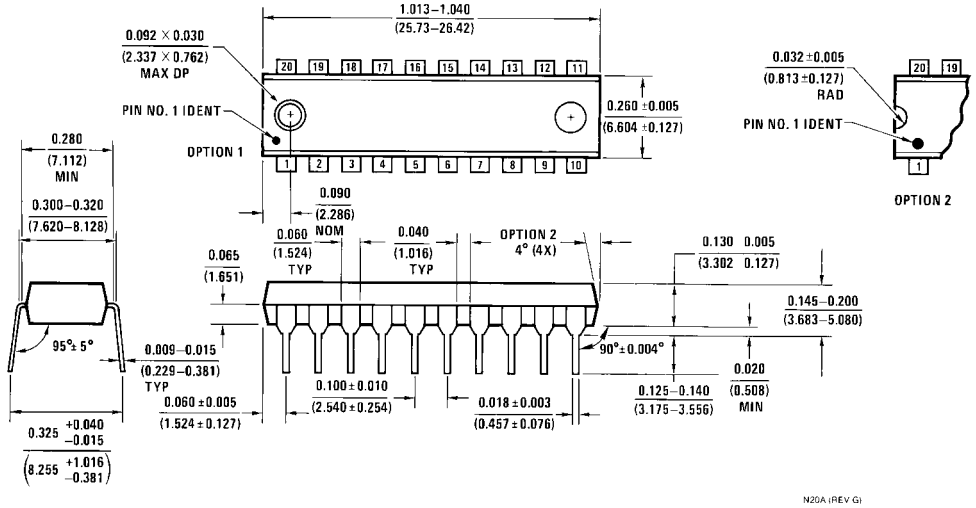
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F243
Quad Bus Transceiver with 3-STATE Outputs

General Description

The 74F243 is a quad bus transmitter/receiver designed for 4-line asynchronous 2-way data communications between data busses.

Features

- 2-Way asynchronous data bus communication
- Input clamp diodes limit high-speed termination effects

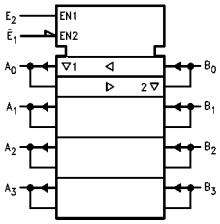
Ordering Code:

Order Code	Package Number	Package Description
74F243SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow

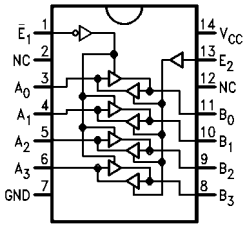
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



Connection Diagram



Truth Table

Inputs		Inputs/Outputs	
$\overline{E}_1$	E_2	A_n	B_n
L	L	Input	B = A
L	H	N/A	N/A
H	L	Z	Z
H	H	A = B	Input

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
N/A = Not Allowed

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{E}_1$	Enable Input (Active LOW)	1.0/1.67	20 µA/–1 mA
E_2	Enable Input (Active HIGH)	1.0/1.67	20 µA/–1 mA
A_n, B_n	Inputs	3.5/2.67	70 µA/–1.6 mA
	Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

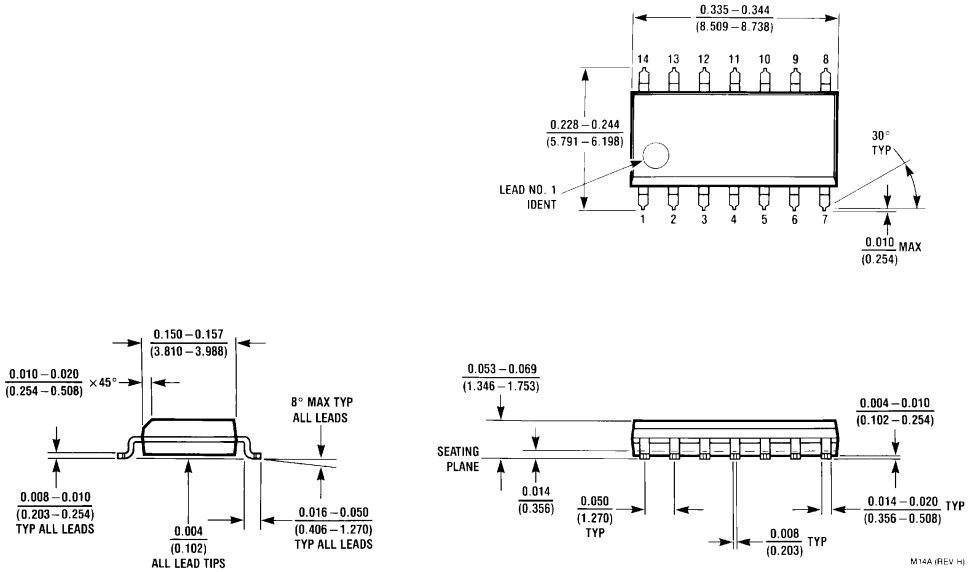
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		10% V_{CC}	2.0					I_{OH} = −15 mA (A_n, B_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V ($\overline{E}_1$, E_2)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.0	mA	Max	V_{IN} = 0.5V ($\overline{E}_1$, E_2)
$I_{IH} + I_{OZH}$	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current				−1.6	mA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CCH}	Power Supply Current			64	80	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			64	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			71	90	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.0	5.2	2.0	6.5	2.0	6.2	ns
t_{PHL}	A_n to B_n, B_n to A_n	2.5	4.0	5.2	2.0	8.5	2.0	6.5	
t_{PZH}	Output Enable Time	2.0	4.3	5.7	2.0	8.0	2.0	6.7	ns
t_{PZL}	$\overline{E}_1$ to B_n, E_2 to A_n	2.0	5.8	7.5	2.0	10.5	2.0	8.5	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	1.5	7.5	1.5	7.0	
t_{PLZ}	$\overline{E}_1$ to B_n, E_2 to A_n	2.0	4.5	6.0	2.0	8.5	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised April 1999

74F245
Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The 74F245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at the A Ports and 64 mA at the B Ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active HIGH) enables data from A Ports to B Ports; Receive (active LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a High Z condition.

Features

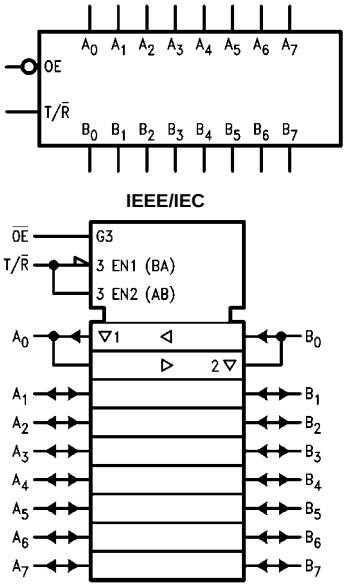
- Non-inverting buffers
- Bidirectional data path
- A outputs sink 24 mA
- B outputs sink 64 mA

Ordering Code:

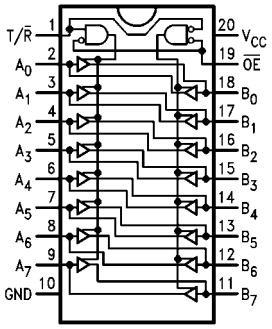
Order Number	Package Number	Package Description
74F245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74F245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/2.0	20 μA/−1.2 mA
$T/\overline{R}$	Transmit/Receive Input	1.0/2.0	20 μA/−1.2 mA
A_0–A_7	Side A Inputs or	3.5/1.083	70 μA/−0.65 mA
	3-STATE Outputs	150/40(38.3)	−3 mA/24 mA (20 mA)
B_0–B_7	Side B Inputs or	3.5/1.083	70 μA/−0.65 mA
	3-STATE Outputs	600/106.6(80)	−12 mA/64 mA (48 mA)

Truth Table

Inputs		Output
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

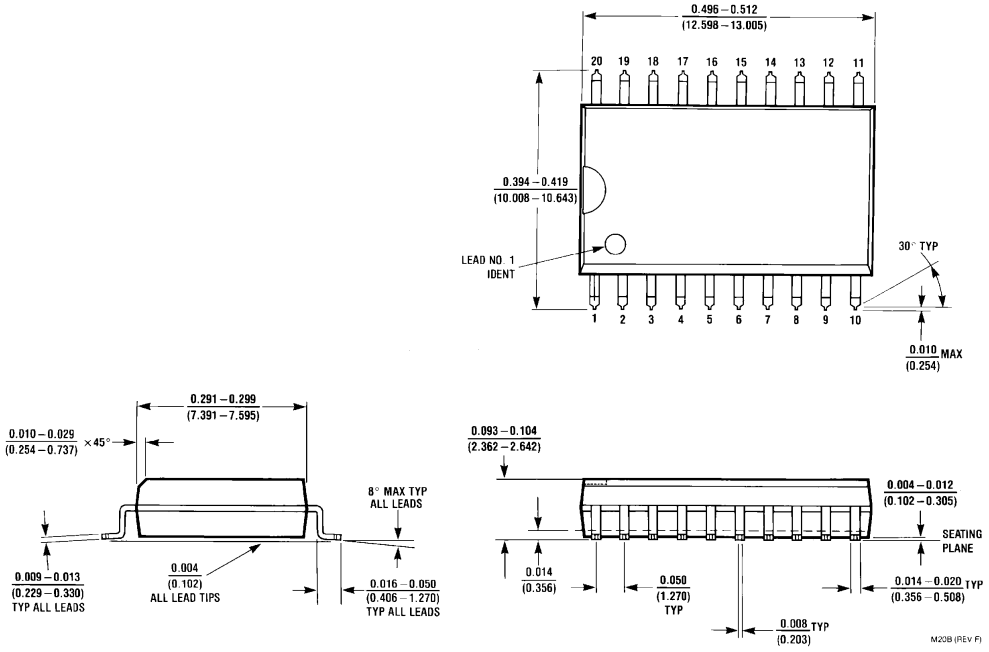
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA (A_n)
		10% V_{CC}	2.0					I_{OH} = −15 mA (B_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA (A_n)
		10% V_{CC}			0.55			I_{OL} = 64 mA (B_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, T/$\overline{R}$)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5 V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.2	mA	Max	V_{IN} = 0.5V (T/$\overline{R}$, $\overline{OE}$)
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V (A_n)
			−100		−225			V_{OUT} = 0V (B_n)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V(A_n, B_n)
I_{CCH}	Power Supply Current			70	90	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			95	120	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			85	110	mA	Max	V_O = HIGH Z

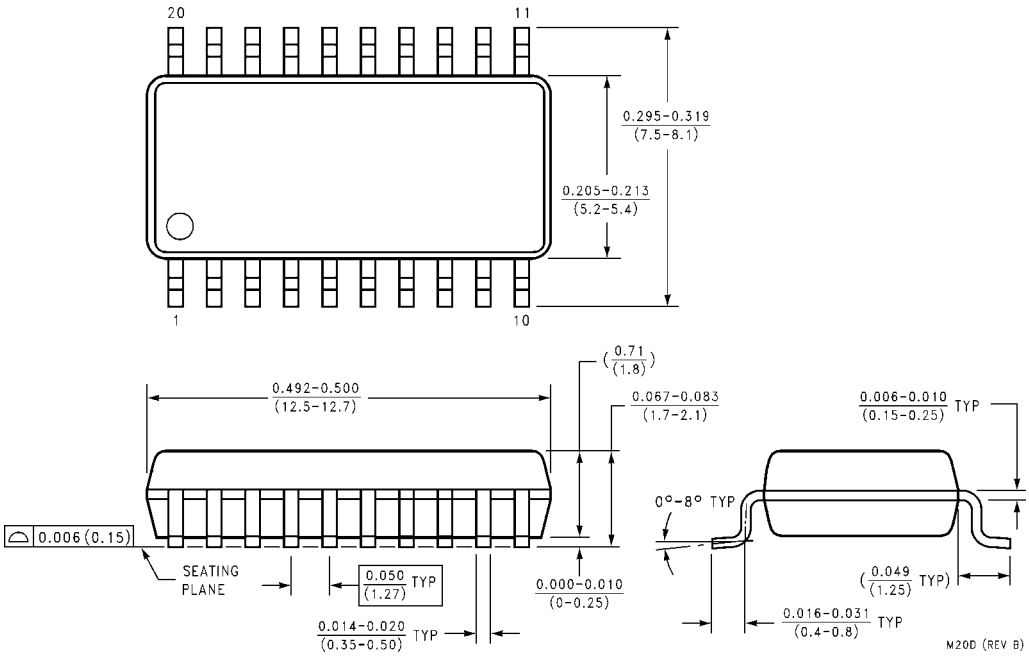
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.2	6.0	2.0	7.5	2.0	7.0	ns
t_{PHL}	A_n to B_n or B_n to A_n	2.5	4.2	6.0	2.0	7.5	2.0	7.0	
t_{PZH}	Output Enable Time	3.0	5.3	7.0	2.5	9.0	2.5	8.0	
t_{PZL}		3.5	6.0	8.0	3.0	10.0	3.0	9.0	ns
t_{PHZ}	Output Disable Time	2.0	5.0	6.5	2.0	9.0	2.0	7.5	
t_{PLZ}		2.0	5.0	6.5	2.0	10.0	2.0	7.5	

Physical Dimensions inches (millimeters) unless otherwise noted

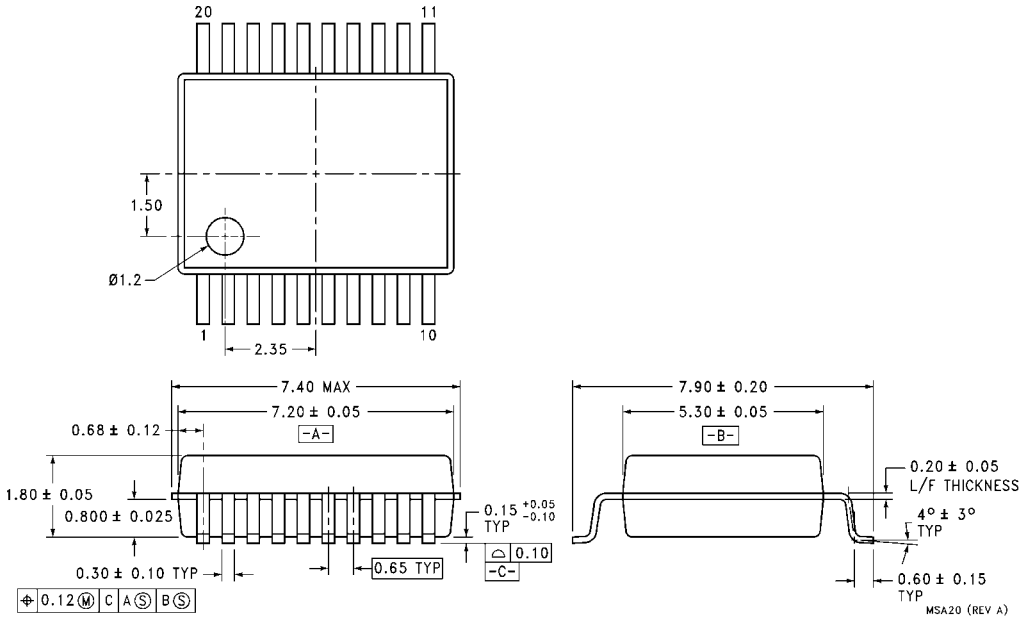


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



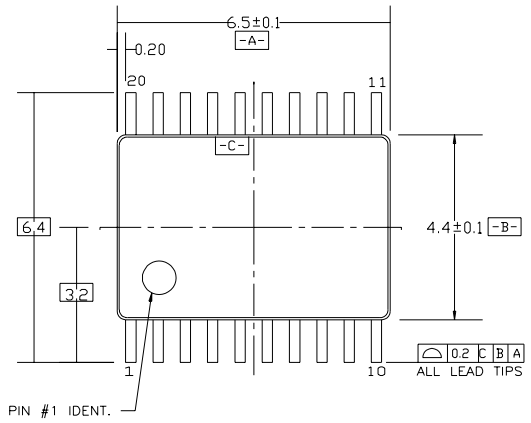
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

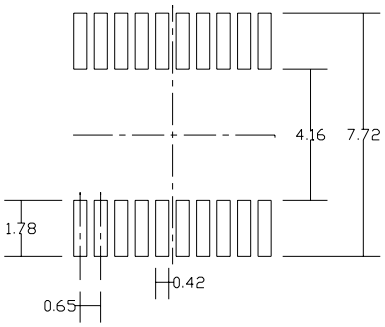
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



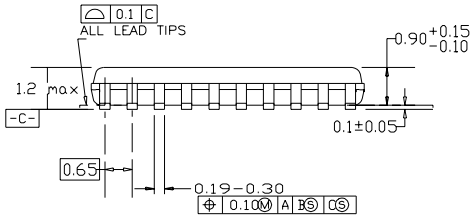
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

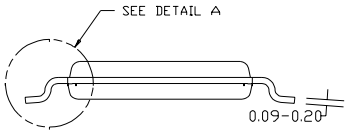
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

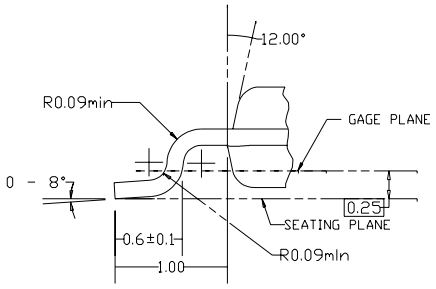




LAND PATTERN RECOMMENDATION







DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

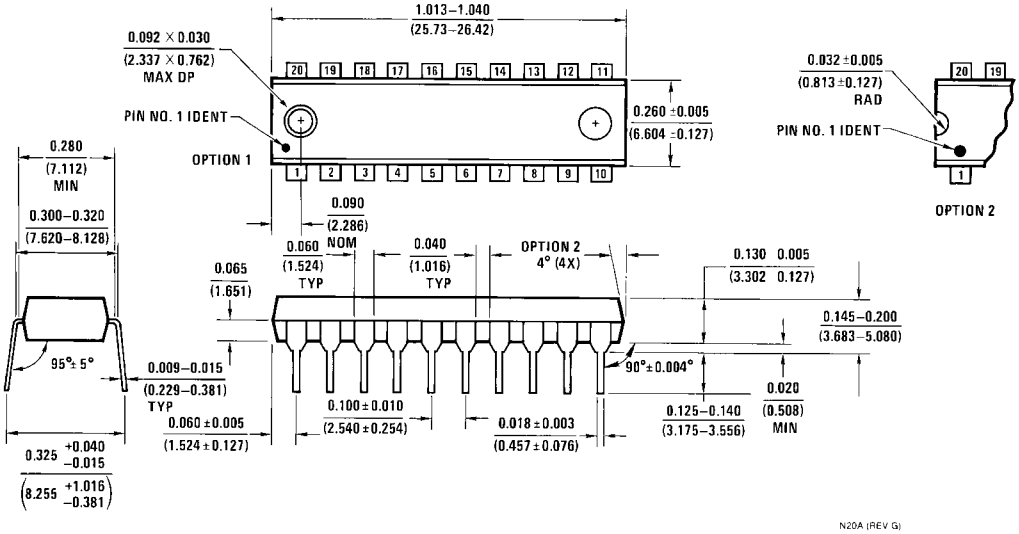
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F251A
8-Input Multiplexer with 3-STATE Outputs

General Description

The 74F251A is a high-speed 8-input digital multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. It can be used as a universal function generator to generate any logic function of four variables. Both assertion and negation outputs are provided.

Features

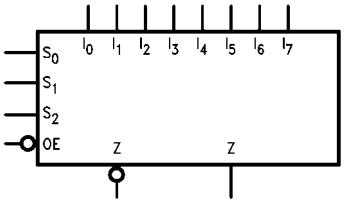
- Multifunctional capability
- On-chip select logic decoding
- Inverting and non-inverting 3-STATE outputs

Ordering Code:

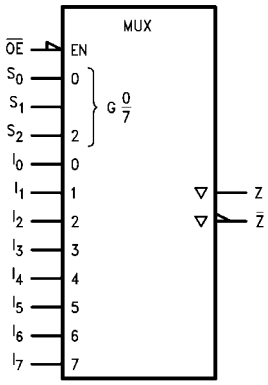
Order Number	Package Number	Package Description
74F251ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F251ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F251APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

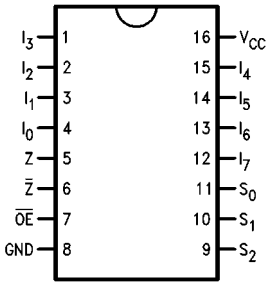
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0–S_2	Select Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
I_0–I_7	Multiplexer Inputs	1.0/1.0	20 µA/–0.6 mA
Z	3-STATE Multiplexer Output	150/40 (33.3)	–3 mA/24 mA (20 mA)
$\overline{Z}$	Complementary 3-STATE Multiplexer Output	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

This device is a logical implementation of a single-pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0, S_1, S_2. Both assertion and negation outputs are provided. The Output Enable input ($\overline{OE}$) is active LOW. When it is activated, the logic function provided at the output is:

$$Z = \overline{OE} \bullet (I_0 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_1 \bullet S_0 \bullet \overline{S}_1 \bullet \overline{S}_2 +$$
$$I_2 \bullet \overline{S}_0 \bullet S_1 \bullet \overline{S}_2 + I_3 \bullet S_0 \bullet S_1 \bullet \overline{S}_2 +$$
$$I_4 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet S_2 + I_5 \bullet S_0 \bullet \overline{S}_1 \bullet S_2 +$$
$$I_6 \bullet \overline{S}_0 \bullet S_1 \bullet S_2 + I_7 \bullet S_0 \bullet S_1 \bullet S_2)$$

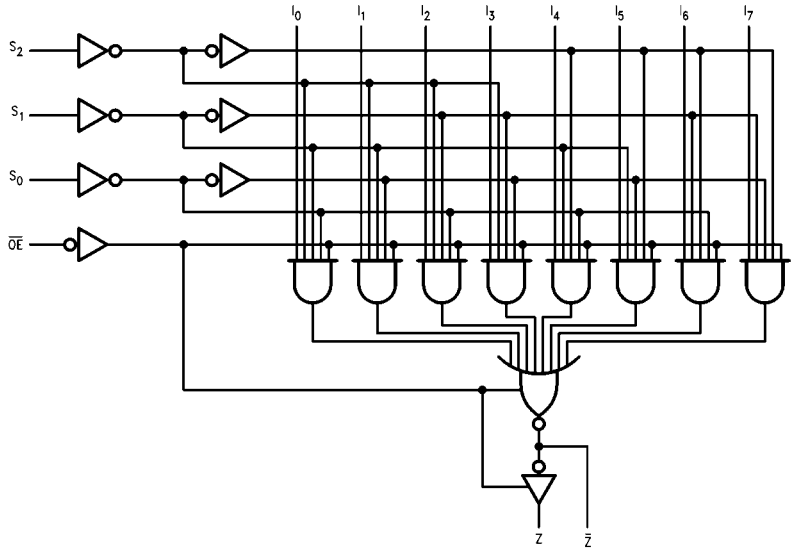
When the Output Enable is HIGH, both outputs are in the high impedance (High Z) state. This feature allows multiplexer expansion by tying the outputs of up to 128 devices together. When the outputs of the 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. The Output Enable signals should be designed to ensure there is no overlap in the active LOW portion of the enable voltages.

Truth Table

Inputs				Outputs	
$\overline{OE}$	S_2	S_1	S_0	$\overline{Z}$	Z
H	X	X	X	Z	Z
L	L	L	L	$\overline{I}_0$	I_0
L	L	L	H	$\overline{I}_1$	I_1
L	L	H	L	$\overline{I}_2$	I_2
L	L	H	H	$\overline{I}_3$	I_3
L	H	L	L	$\overline{I}_4$	I_4
L	H	L	H	$\overline{I}_5$	I_5
L	H	H	L	$\overline{I}_6$	I_6
L	H	H	H	$\overline{I}_7$	I_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

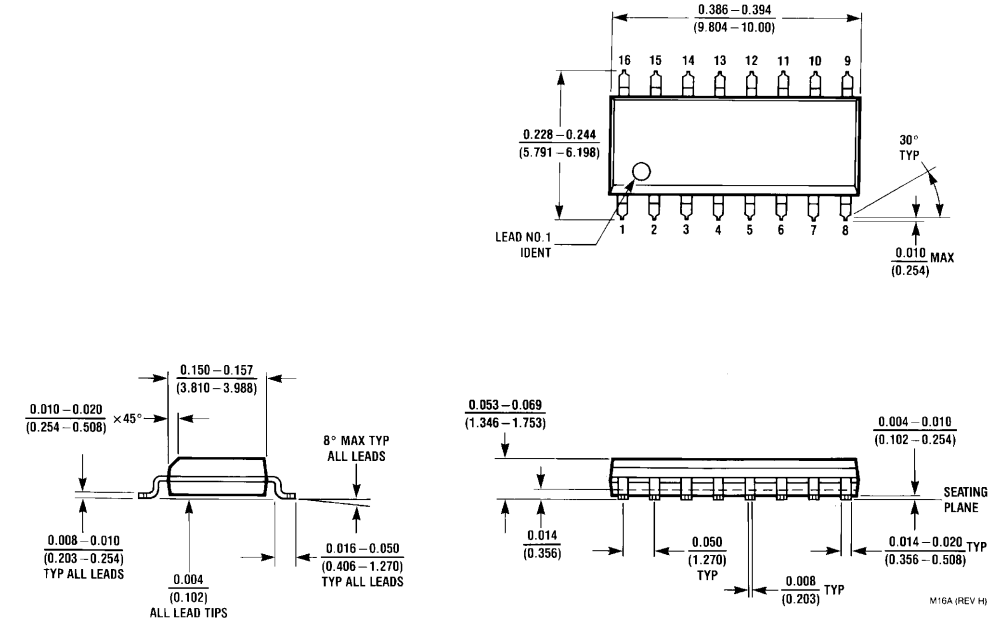
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCL}	Power Supply Current			15	22	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			16	24	mA	Max	V_O = HIGH Z

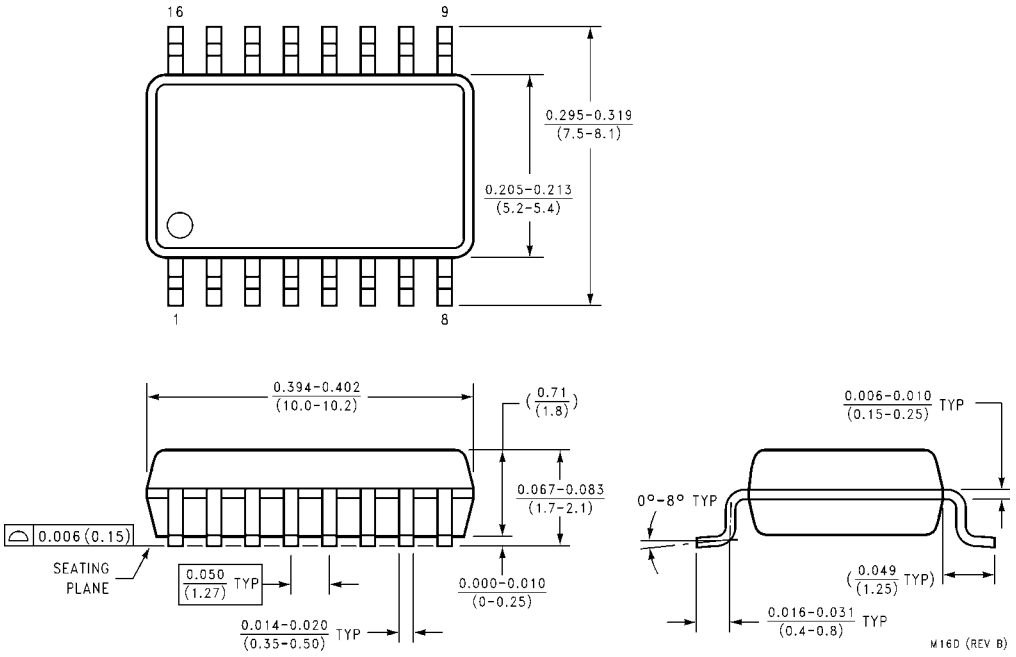
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.5	6.0	9.0	3.5	11.5	3.5	9.5	ns
t_{PHL}	S_n to $\overline{Z}$	3.2	5.0	7.5	3.2	8.0	3.2	7.5	
t_{PLH}	Propagation Delay	4.5	7.5	10.5	3.5	14.0	4.5	12.5	ns
t_{PHL}	S_n to Z	4.0	6.0	8.5	3.0	10.5	4.0	9.0	
t_{PLH}	Propagation Delay	3.0	5.0	6.5	2.5	8.0	3.0	7.0	ns
t_{PHL}	I_n to $\overline{Z}$	1.5	2.5	4.0	1.5	6.0	1.5	5.0	
t_{PLH}	Propagation Delay	3.5	5.0	7.0	2.5	9.0	2.5	8.0	ns
t_{PHL}	I_n to Z	3.5	5.5	7.0	3.5	9.0	3.5	7.5	
t_{PZH}	Output Enable Time	2.5	4.3	6.0	2.0	7.0	2.5	7.0	ns
t_{PZL}	$\overline{OE}$ to $\overline{Z}$	2.5	4.3	6.0	2.5	7.5	2.5	6.5	
t_{PHZ}	Output Disable Time	2.5	4.0	5.5	2.5	6.0	2.5	6.0	
t_{PLZ}	$\overline{OE}$ to $\overline{Z}$	1.5	3.0	4.5	1.5	5.0	1.5	4.5	
t_{PZH}	Output Enable Time	3.5	5.0	7.0	3.0	8.5	3.0	7.5	ns
t_{PZL}	$\overline{OE}$ to Z	3.5	5.5	7.5	3.5	9.0	3.5	8.0	
t_{PHZ}	Output Disable Time	2.0	3.8	5.5	2.0	5.5	2.0	5.5	
t_{PLZ}	$\overline{OE}$ to Z	1.5	3.0	4.5	1.5	5.5	1.5	4.5	

Physical Dimensions inches (millimeters) unless otherwise noted

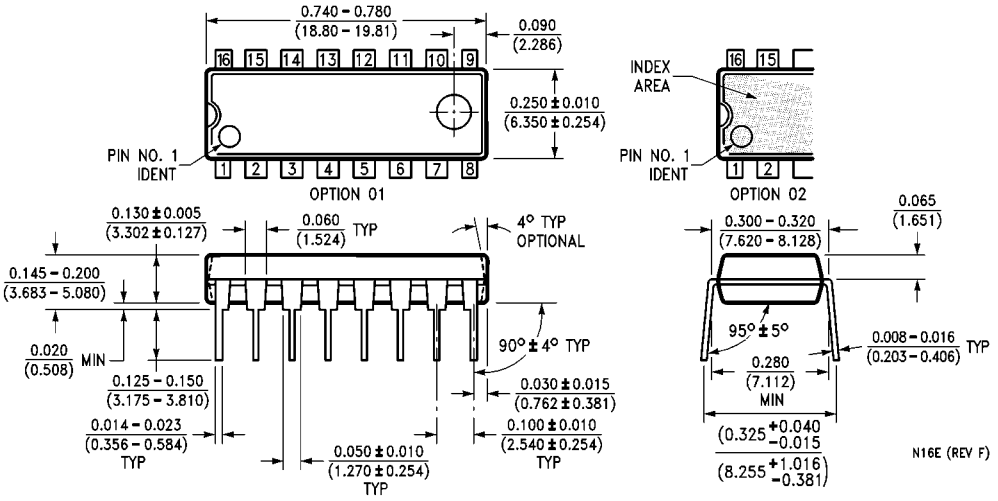


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F253
Dual 4-Input Multiplexer with 3-STATE Outputs

General Description

The 74F253 is a dual 4-input multiplexer with 3-STATE outputs. It can select two bits of data from four sources using common select inputs. The output may be individually switched to a high impedance state with a HIGH on the respective Output Enable ($\overline{OE}$) inputs, allowing the outputs to interface directly with bus oriented systems.

Features

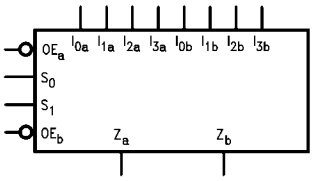
- Multifunction capability
- Non-inverting 3-STATE outputs

Ordering Code:

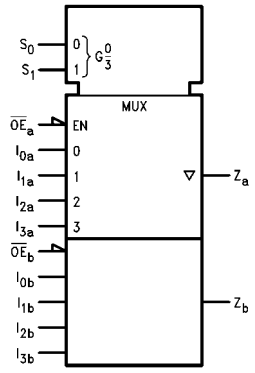
Order Number	Package Number	Package Description
74F253SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F253SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F253PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

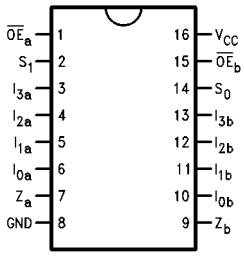
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_{0a}–I_{3a}	Side A Data Inputs	1.0/1.0	20 μA/–0.6 mA
I_{0b}–I_{3b}	Side B Data Inputs	1.0/1.0	20 μA/–0.6 mA
S_0–S_1	Common Select Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}_a$	Side A Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}_b$	Side B Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
Z_a, Z_b	3-STATE Outputs	150/40(33.3)	–3 mA/24 mA (20 mA)

Functional Description

This device contains two identical 4-input multiplexers with 3-STATE outputs. They select two bits from four sources selected by common Select inputs (S_0, S_1). The 4-input multiplexers have individual Output Enable ($\overline{OE}_a$, $\overline{OE}_b$) inputs which, when HIGH, force the outputs to a high impedance (High Z) state. This device is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two select inputs. The logic equations for the outputs are shown below:

$$Z_a = \overline{OE}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0)$$

$$Z_b = \overline{OE}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet S_0 + I_{3b} \bullet S_1 \bullet S_0)$$

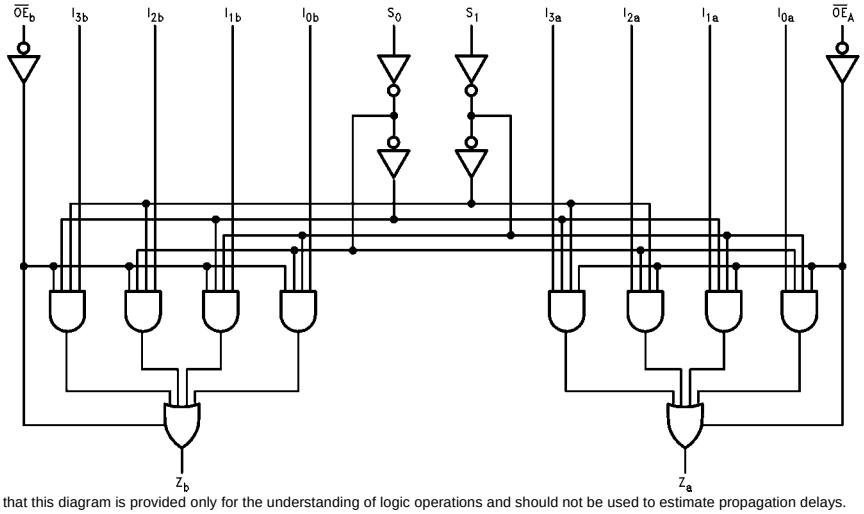
If the outputs of 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-STATE devices whose outputs are tied together are designed so that there is no overlap.

Truth Table

Select Inputs		Data Inputs				Output Enable	Output
S_0	S_1	I_0	I_1	I_2	I_3	$\overline{OE}$	$\overline{Z}$
X	X	X	X	X	X	H	Z
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
H	L	X	L	X	X	L	L
H	L	X	H	X	X	L	H
L	H	X	X	L	X	L	L
L	H	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Address inputs S_0 and S_1 are common to both sections.
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

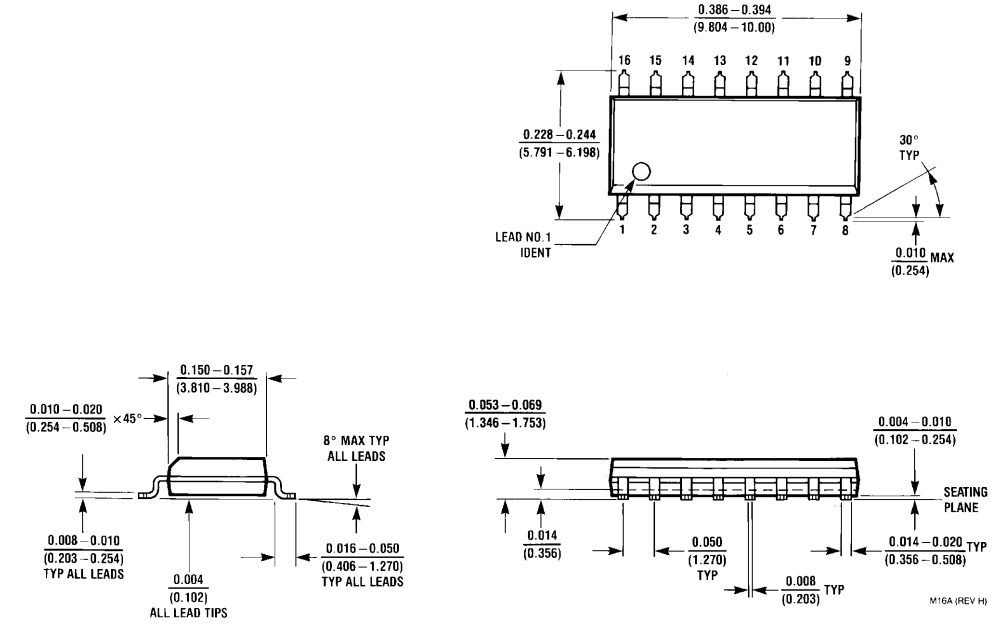
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
			−100		−225			V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current			11.5	16	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			16	23	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			16	23	mA	Max	V_O = HIGH Z

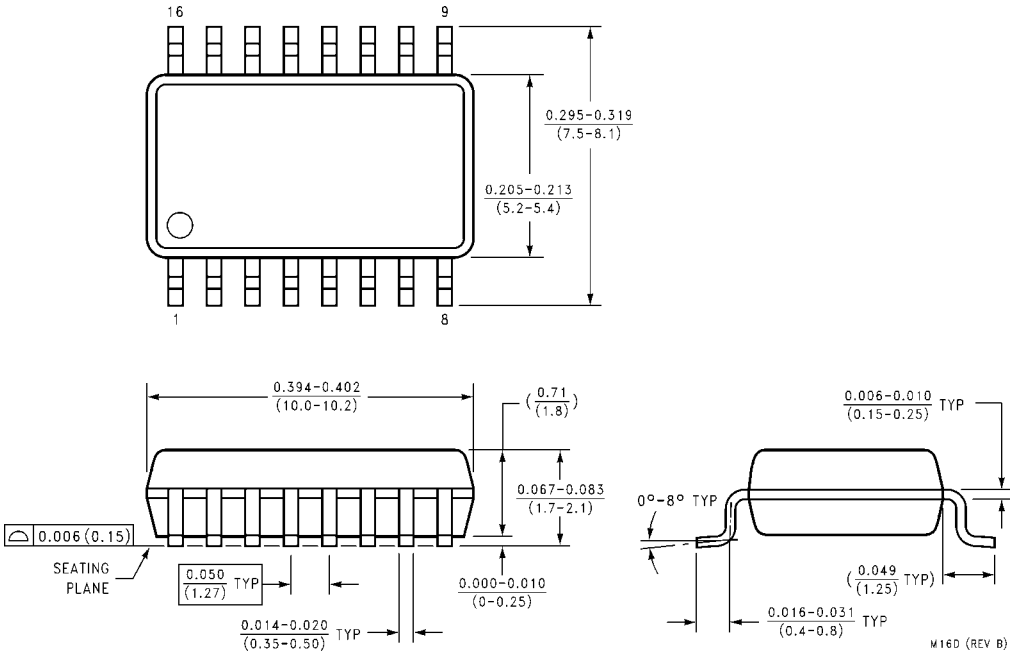
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	4.5	8.5	11.5	3.5	15.0	4.5	13.0	ns
t_{PHL}	S_n to Z_n	3.0	6.5	9.0	2.5	11.0	3.0	10.0	
t_{PLH}	Propagation Delay	3.0	5.5	7.0	2.5	9.0	3.0	8.0	ns
t_{PHL}	I_n to Z_n	2.5	4.5	6.0	2.5	8.0	2.5	7.0	
t_{PZH}	Output Enable Time	3.0	6.0	8.0	2.5	10.0	3.0	9.0	ns
t_{PZL}		3.0	6.0	8.0	2.5	10.0	3.0	9.0	
t_{PHZ}	Output Disable Time	2.0	3.7	5.0	2.0	6.5	2.0	6.0	
t_{PLZ}		2.0	4.4	6.0	2.0	8.0	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted

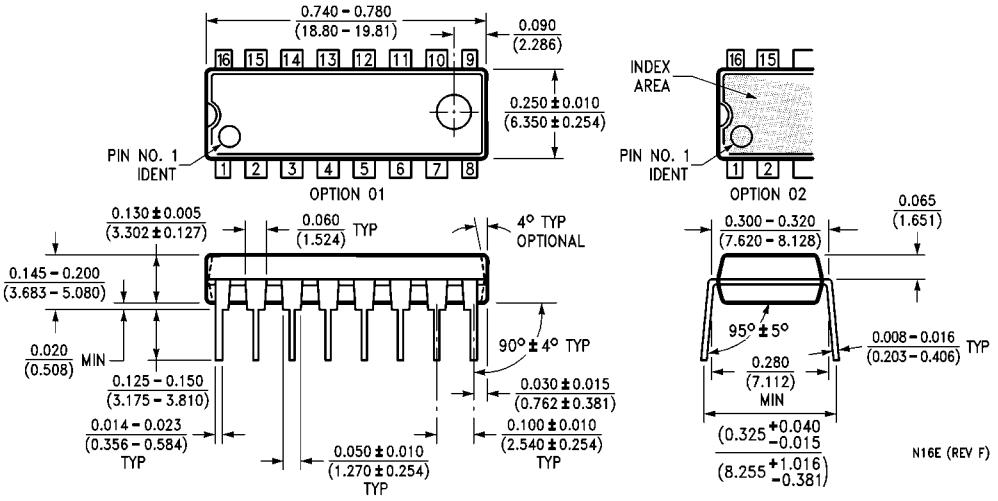


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F257A
Quad 2-Input Multiplexer with 3-STATE Outputs

General Description

The 74F257A is a quad 2-input multiplexer with 3-STATE outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (non-inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ($\overline{OE}$) input, allowing the outputs to interface directly with bus-oriented systems.

Features

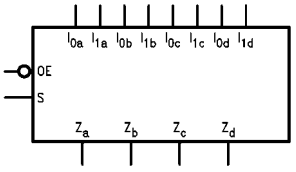
- Multiplexer expansion by tying outputs together
- Non-inverting 3-STATE outputs
- Input clamp diodes limit high-speed termination effects

Ordering Code:

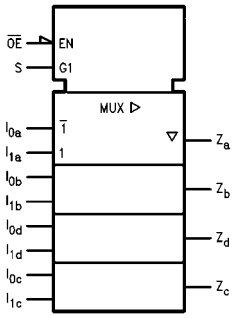
Order Number	Package Number	Package Description
74F257ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F257ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F257APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

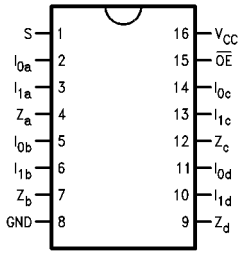
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S	Common Data Select Input	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
I_{0a}–I_{0d}	Data Inputs from Source 0	1.0/1.0	20 µA/–0.6 mA
I_{1a}–I_{1d}	Data Inputs from Source 1	1.0/1.0	20 µA/–0.6 mA
Z_a–Z_d	3-STATE Multiplexer Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Truth Table

Output Enable	Select Input	Data Inputs		Output
$\overline{OE}$	S	I_0	I_1	Z
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

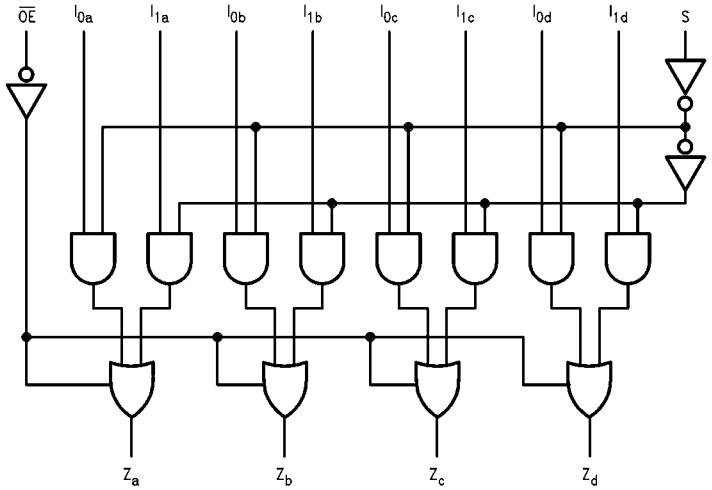
Functional Description

The 74F257A is a quad 2-input multiplexer with 3-STATE outputs. It selects four bits of data from two sources under control of a Common Data Select input. When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The data on the selected inputs appears at the outputs in true (non-inverted) form. The device is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equation for the outputs is shown below:

$$Z_n = \overline{OE} \bullet (I_n \bullet S + I_{on} \bullet \overline{S})$$

When the Output Enable input ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance OFF state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure the Output Enable signals to 3-STATE devices whose outputs are tied together are designed so there is no overlap.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

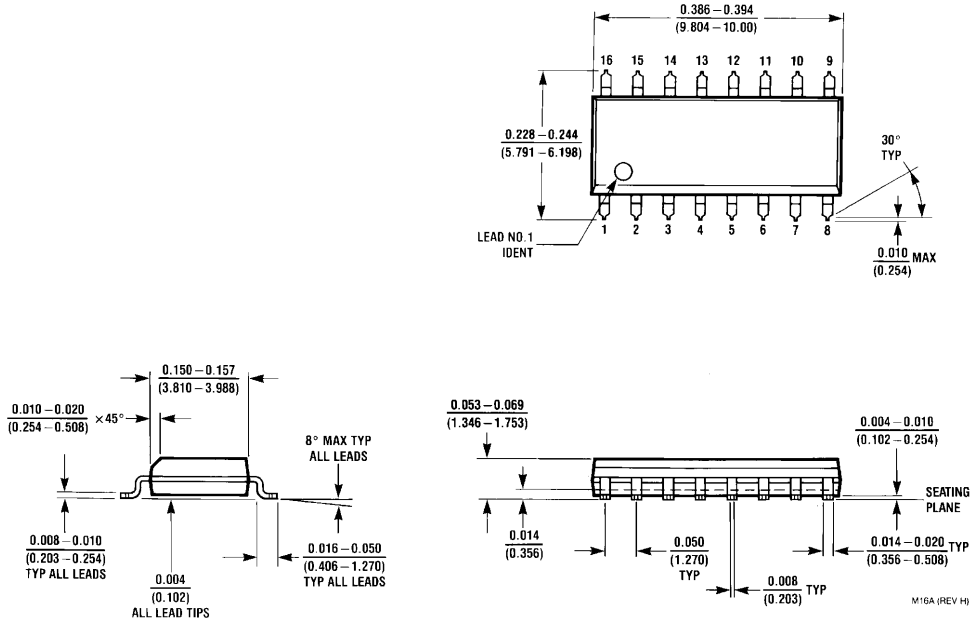
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			9.0	15	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			14.5	22	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			15	23	mA	Max	V_O = HIGH Z

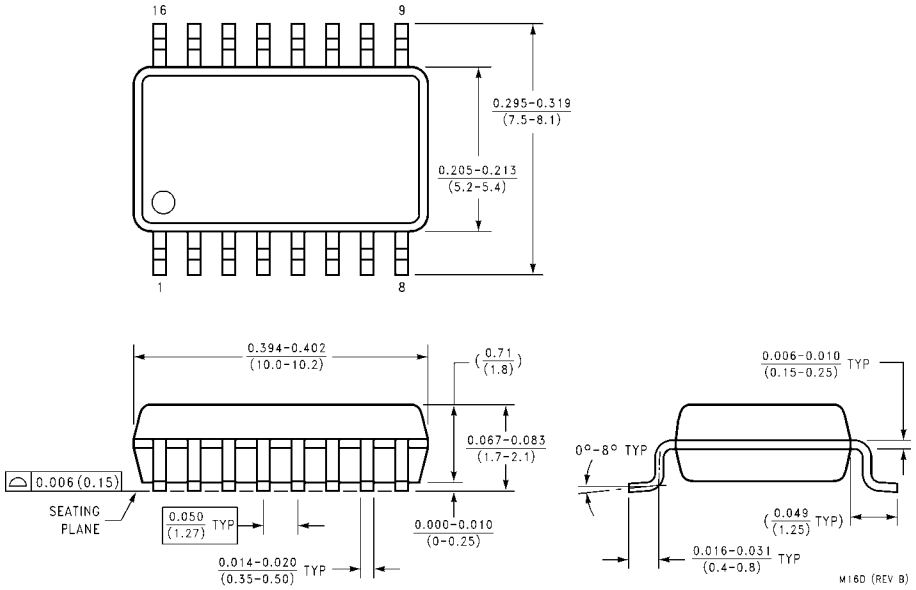
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.5	5.5	2.0	7.0	2.0	6.0	ns
t_{PHL}	I_n to Z_n	2.0	4.2	5.5	1.5	7.0	2.0	6.0	
t_{PLH}	Propagation Delay	4.0	5.0	9.5	3.5	11.5	3.5	10.5	ns
t_{PHL}	S to Z_n	2.5	6.5	7.0	2.5	9.0	2.5	8.0	
t_{PZH}	Output Enable Time	2.0	5.9	6.0	2.0	8.0	2.0	7.0	ns
t_{PZL}		2.5	5.5	7.0	2.5	9.0	2.5	8.0	
t_{PHZ}	Output Disable Time	2.0	4.3	6.0	2.0	7.0	2.0	7.0	
t_{PLZ}		2.0	4.5	6.0	2.0	8.5	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted

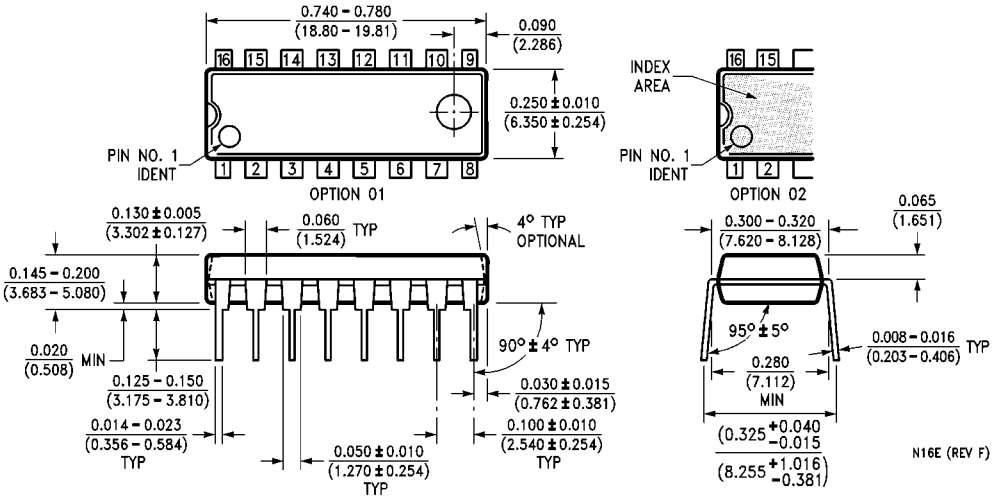


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F258A
Quad 2-Input Multiplexer with 3-STATE Outputs

General Description

The 74F258A is a quad 2-input multiplexer with 3-STATE outputs. Four bits of data from two sources can be selected using a common data select input. The four outputs present the selected data in the complement (inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ($\overline{OE}$) input, allowing the outputs to interface directly with bus-oriented systems.

Features

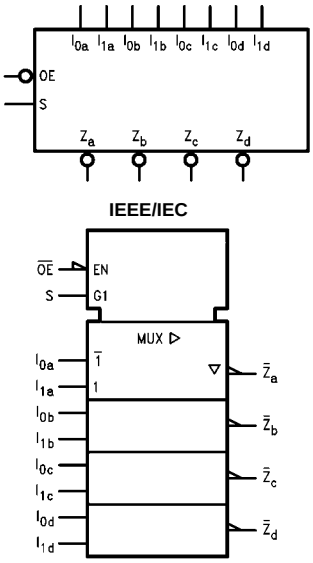
- Multiplexer expansion by tying outputs together
- Inverting 3-STATE outputs

Ordering Code:

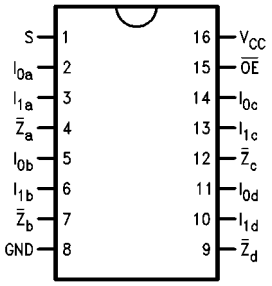
Order Number	Package Number	Package Description
74F258ASC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F258ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F258APC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S	Common Data Select Input	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
I_{0a}–I_{0d}	Data Inputs from Source 0	1.0/1.0	20 μA/–0.6 mA
I_{1a}–I_{1d}	Data Inputs from Source 1	1.0/1.0	20 μA/–0.6 mA
$\overline{Z}_a$–$\overline{Z}_d$	3-STATE Inverting Data Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Truth Table

Output Enable	Select Input	Data Inputs		Output
$\overline{OE}$	S	I_0	I_1	$\overline{Z}$
H	X	X	X	Z
L	H	X	L	H
L	H	X	H	L
L	L	L	X	H
L	L	H	X	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

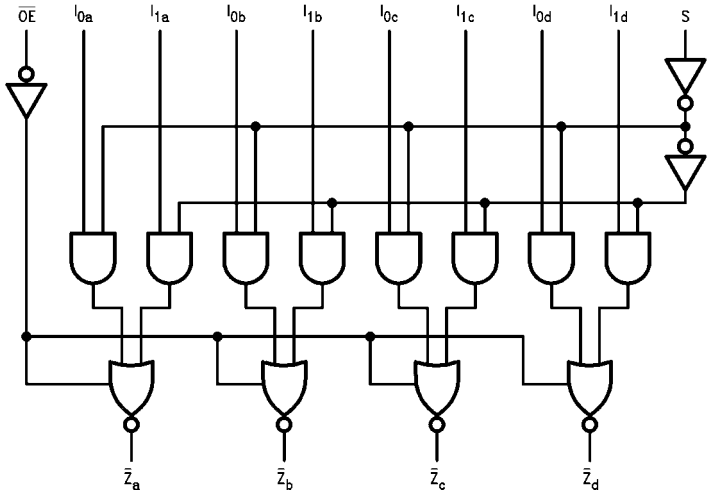
Functional Description

The 74F258A is a quad 2-input multiplexer with 3-STATE outputs. It selects four bits of data from two sources under control of a common Select input (S). When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The data on the selected inputs appears at the outputs in inverted form. The 74F258A is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equation for the outputs is shown below:

$$\overline{Z}_n = \overline{OE} \bullet (I_{1n} \bullet S + I_{0n} \bullet \overline{S})$$

When the Output Enable input ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance OFF state. If the outputs of the 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-STATE devices whose outputs are tied together are designed so there is no overlap.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

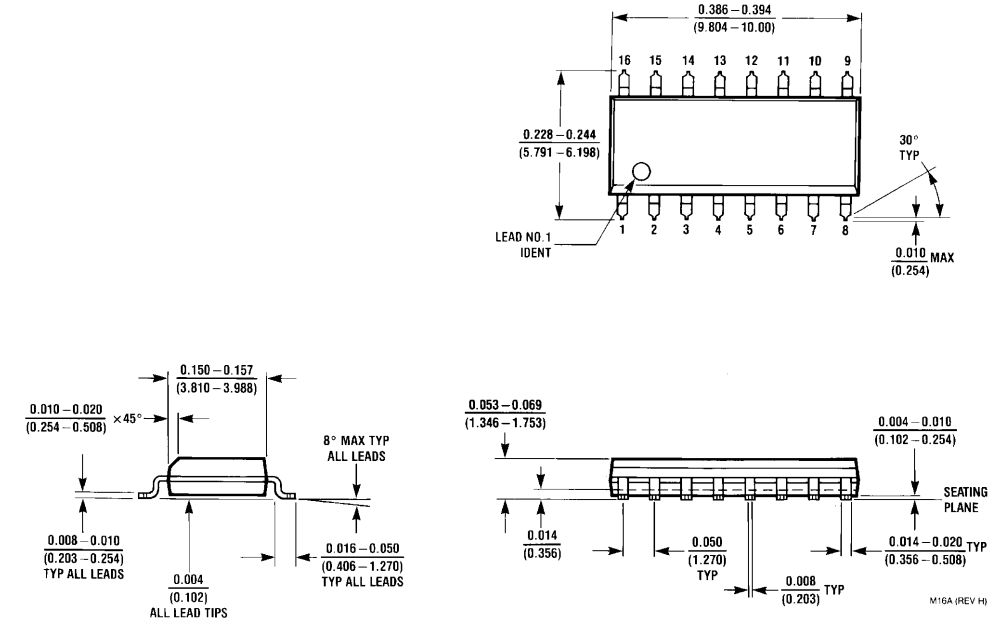
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current			6.2	9.5	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			15.1	23	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			11.3	17	mA	Max	V_O = HIGH Z

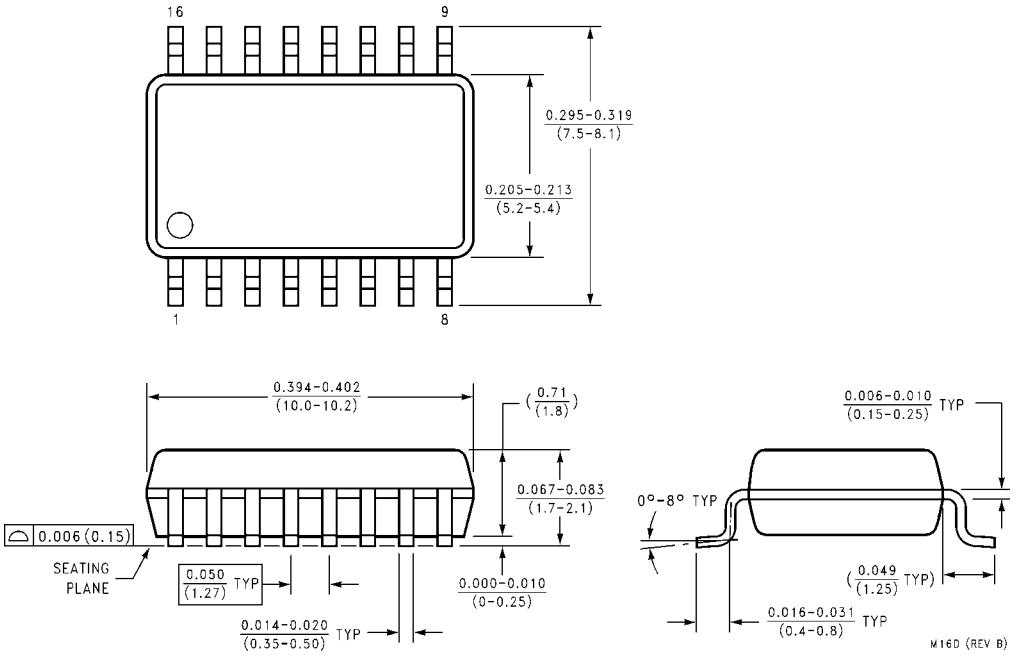
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -5°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5		5.3	2.0	7.5	2.0	6.0	ns
t_{PHL}	I_n to $\overline{Z}_n$	1.0		4.0	1.0	6.0	1.0	5.0	
t_{PLH}	Propagation Delay	3.0		7.5	3.0	9.5	3.0	8.5	ns
t_{PHL}	S to $\overline{Z}_n$	2.5		7.0	2.5	9.0	2.5	8.0	
t_{PZH}	Output Enable Time	2.0		6.0	2.0	8.0	2.0	7.0	ns
t_{PZL}		2.5		7.0	2.5	9.0	2.5	8.0	
t_{PHZ}	Output Disable Time	2.0		6.0	1.5	7.0	2.0	7.0	
t_{PLZ}		2.0		6.0	2.0	8.5	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted

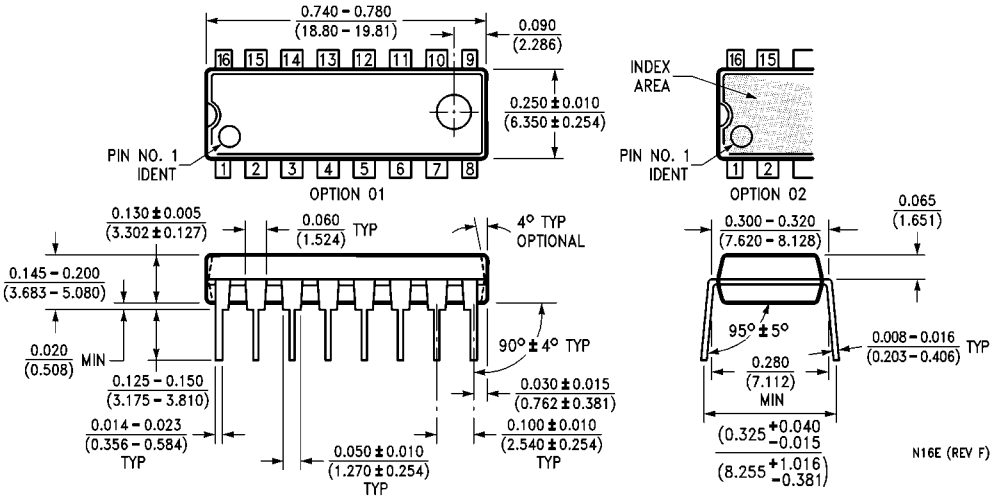


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1989
Revised August 1999

74F2645
Octal Bus Transceiver with 25Ω Series Resistors in the Outputs

General Description

This device is an octal bus transceiver designed for asynchronous two-way data flow between the A and B busses and is functionally equivalent to the 74F645. The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors. Both busses are capable of sinking 12 mA, sourcing 15 mA, have 3-STATE outputs, and a common output enable pin. The direction of data flow is determined by the transmit/receive ($T/\overline{R}$) input. The 74F2645 is a low power version of the 74F245 with 25Ω series resistors in the outputs.

Features

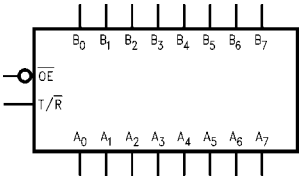
- 25Ω series resistors in the outputs eliminates the need for external resistors
- Designed for asynchronous two-way data flow between busses
- Outputs sink 12 mA and source 15 mA
- Transmit/receive ($T/\overline{R}$) input controls the direction of data flow
- 74F2645 is a low power version of the 74F245 with 25Ω series resistors in the outputs

Ordering Code:

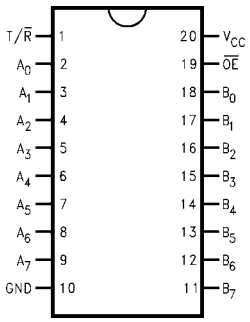
Order Number	Package Number	Package Description
74F2645SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



FAST® is a registered trademark of Fairchild Semiconductor Corporation.

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
T/$\overline{R}$	Transmit/Receive Input	1.0/1.0	20 μA/–0.6 mA
A_0–A_7	Side A Inputs or	3.5/0.667	70 μA/–0.4 mA
	3-STATE Outputs	750/20	–15 mA/12 mA
B_0–B_7	Side B Inputs or	3.5/0.667	70 μA/–0.4 mA
	3-STATE Outputs	750/20	–15 mA/12 mA

Functional Description

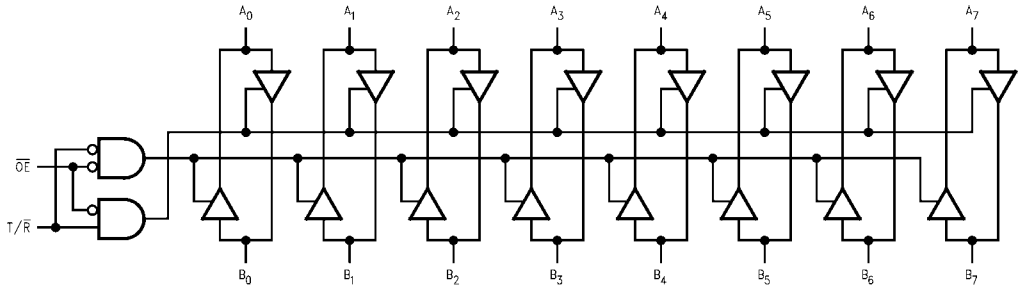
The output enable ($\overline{OE}$) is active LOW. If the device is disabled ($\overline{OE}$ HIGH), the outputs are in the high impedance state. The transmit/receive input (T/$\overline{R}$) controls whether data is transmitted from the A bus to the B bus or from the B bus to the A bus. When T/$\overline{R}$ is LOW, B data is sent to the A bus. If T/$\overline{R}$ is HIGH, A data is sent to the B bus.

Function Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B data to Bus A
L	H	Bus A data to Bus B
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High Impedance State

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

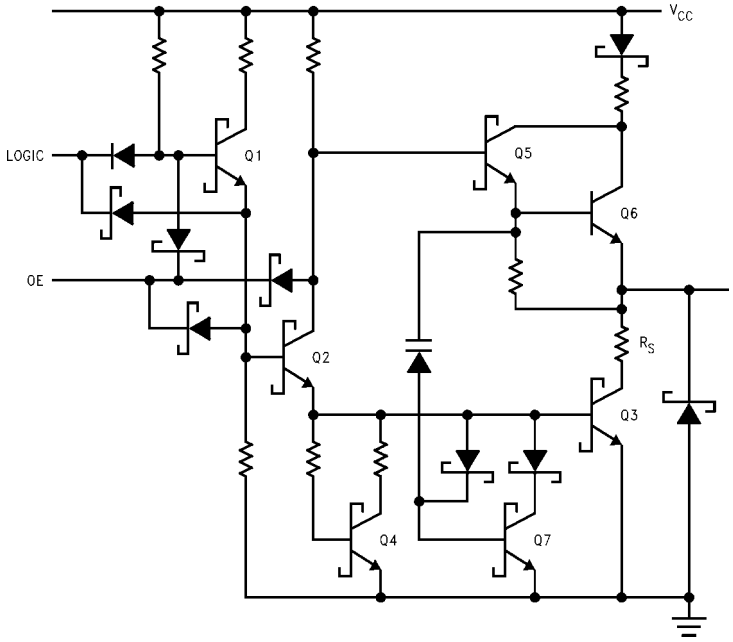
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.50	V	Min	I_{OL} = 1 mA (A_n, B_n)
		10% V_{CC}			0.75			I_{OL} = 12 mA (A_n, B_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V (Non I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (Non I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25
I_{CCL}	Power Supply Current (74F2645)				82	mA	Max	V_O = LOW, V_{IN} = 0.2V
I_{CCZ}	Power Supply Current (74F2645)				95	mA	Max	V_O = HIGH Z

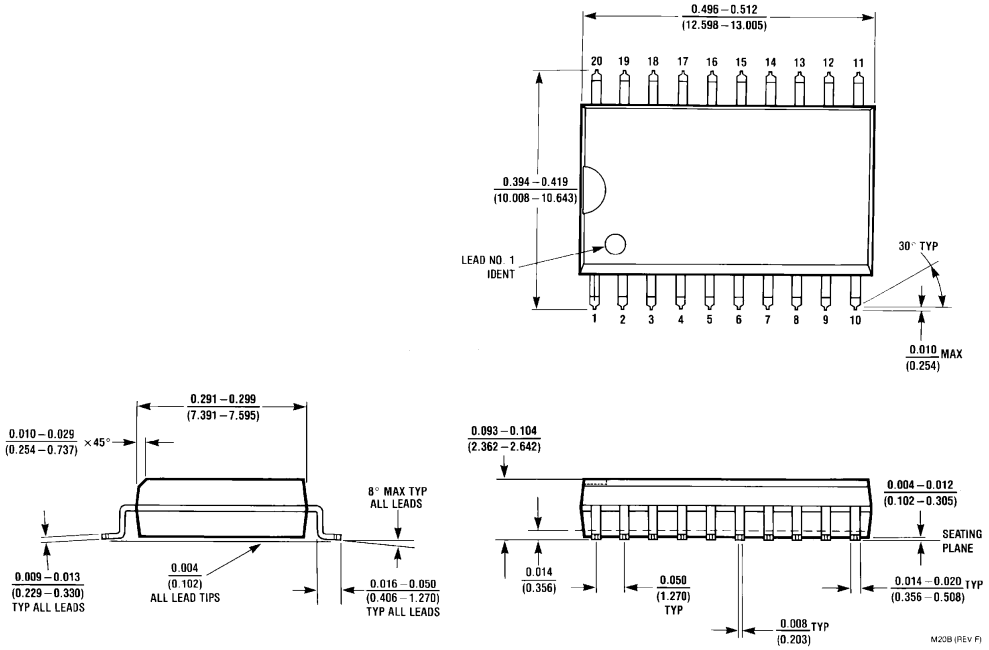
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5		6.0	1.5	7.0	ns
t_{PHL}	A Input to B Output	2.5		7.5	2.5	8.0	
t_{PLH}	Propagation Delay	1.5		6.0	1.5	7.0	ns
t_{PHL}	B Input to A Output	2.5		7.5	2.5	8.0	
t_{PZH}	Enable Time	2.5		8.0	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ Input to A Output	2.5		8.5	2.0	8.5	
t_{PHZ}	Disable Time	1.5		7.0	1.0	8.0	
t_{PLZ}	$\overline{OE}$ Input to A Output	1.0		5.5	1.0	5.5	
t_{PZH}	Enable Time	2.5		7.5	2.0	9.5	ns
t_{PZL}	$\overline{OE}$ Input to B Output	2.5		8.5	2.5	9.0	
t_{PHZ}	Disable Time	1.5		6.5	1.0	7.5	
t_{PLZ}	$\overline{OE}$ Input to B Output	1.0		6.5	1.0	6.5	

Basic FAST Circuit Showing Series Resistor Placement



Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F269
8-Bit Bidirectional Binary Counter

General Description

The 74F269 is a fully synchronous 8-stage up/down counter featuring a preset capability for programmable operation, carry lookahead for easy cascading and a U/$\overline{D}$ input to control the direction of counting. All state changes, whether in counting or parallel loading, are initiated by the rising edge of the clock.

Features

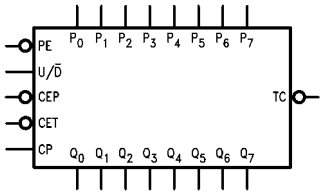
- Synchronous counting and loading
- Built-in lookahead carry capability
- Count frequency 100 MHz
- Supply current 113 mA typ
- 300 mil slimline package

Ordering Code:

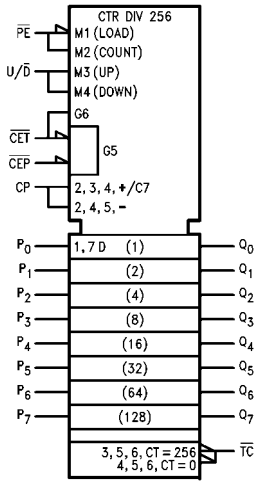
Order Number	Package Number	Package Description
74F269SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F269SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

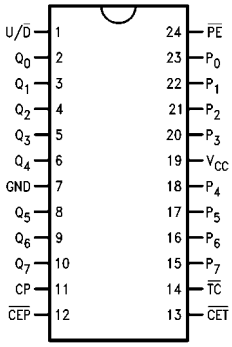
Logic Symbols



IEEE/IEC



Connection Diagram



Function Table

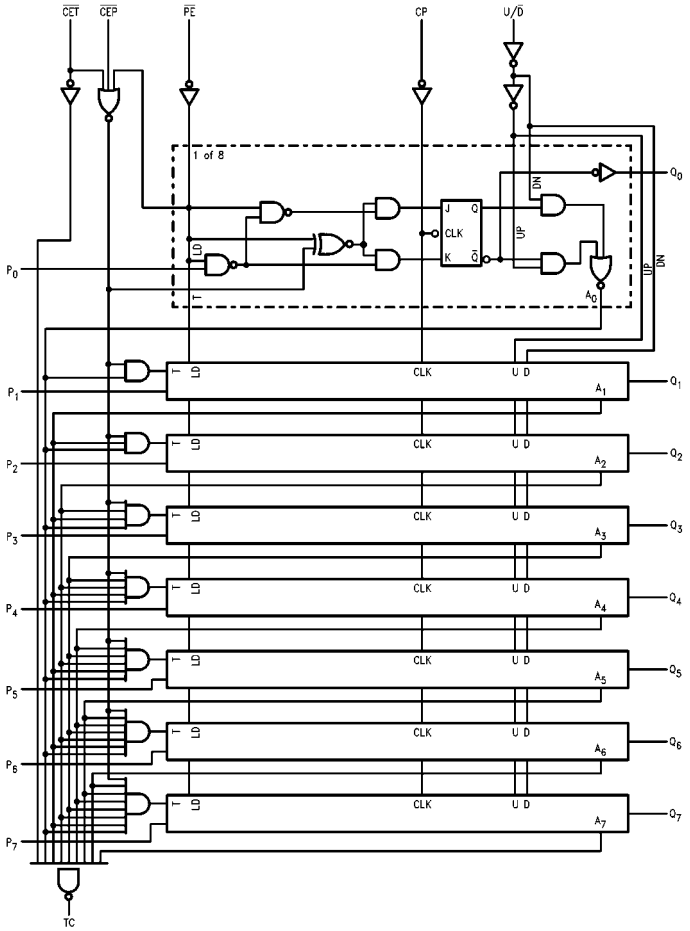
$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	U/$\overline{D}$	CP	Function
L	X	X	X	⌐	Parallel Load All Flip-Flops
H	H	X	X	⌐	Hold
H	X	H	X	⌐	Hold ($\overline{TC}$ Held HIGH)
H	L	L	H	⌐	Count Up
H	L	L	L	⌐	Count Down

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = Transition LOW-to-HIGH

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
P_0–P_7	Parallel Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{PE}$	Parallel Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
U/$\overline{D}$	Up-Down Count Control Input	1.0/1.0	20 µA/–0.6 mA
$\overline{CEP}$	Count Enable Parallel Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{CET}$	Count Enable Trickle Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
CP	Clock Input	1.0/1.0	20 µA/–0.6 mA
$\overline{TC}$	Terminal Count Output (Active LOW)	5.0/33.3	–1 mA/20 mA
Q_0–Q_7	Flip-Flop Outputs	50/33.3	–1 mA/20 mA

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			104	125	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			113	135	mA	Max	V_O = LOW

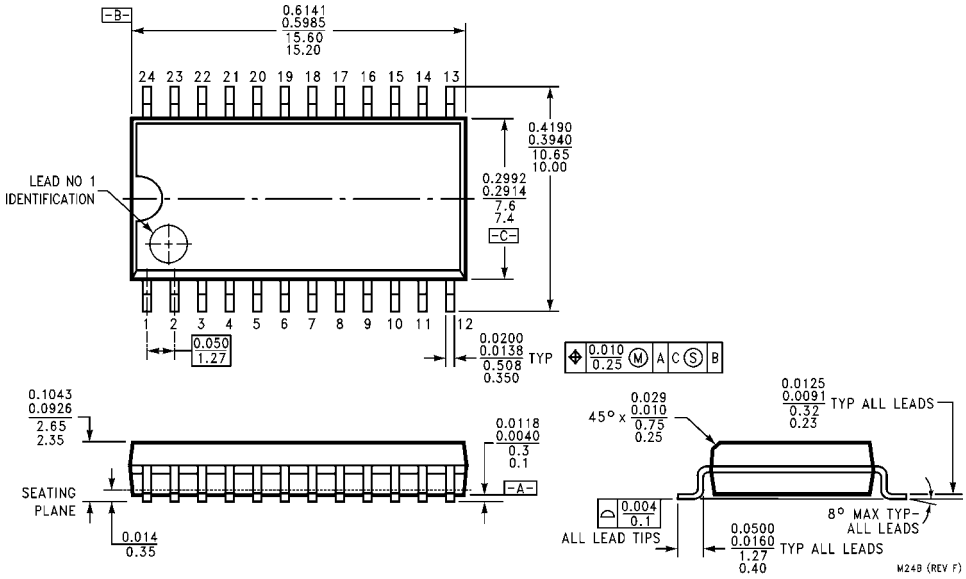
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100			85		MHz
t_{PLH}	Propagation Delay	3.5		8.0	3.5	7.0	ns
t_{PHL}	CP to Q_n (Count-Up)	4.5		10.5	4.5	11.0	
t_{PLH}	Propagation Delay	3.5		7.5	3.5	10.0	ns
t_{PHL}	U/$\overline{D}$ to $\overline{TC}$	4.5		7.5	4.5	11.0	
t_{PLH}	Propagation Delay	3.5		7.0	3.5	10.5	ns
t_{PHL}	$\overline{CET}$ to $\overline{TC}$	3.0		10.5	3.0	11.5	
t_{PLH}	Propagation Delay	4.5		10.0	4.5	10.5	ns
t_{PHL}	CP to $\overline{TC}$	5.0		10.0	4.5	10.5	
t_{PLH}	Propagation Delay	3.5		10.5	3.5	11.0	ns
t_{PHL}	CP to Q_n (Count-Down)	4.5		10.5	4.5	11.0	
t_{PLH}	Propagation Delay	3.5		7.0	3.5	10.0	ns
t_{PHL}	CP to Q_n (Load)	4.0		7.0	4.0	7.0	

AC Operating Requirements

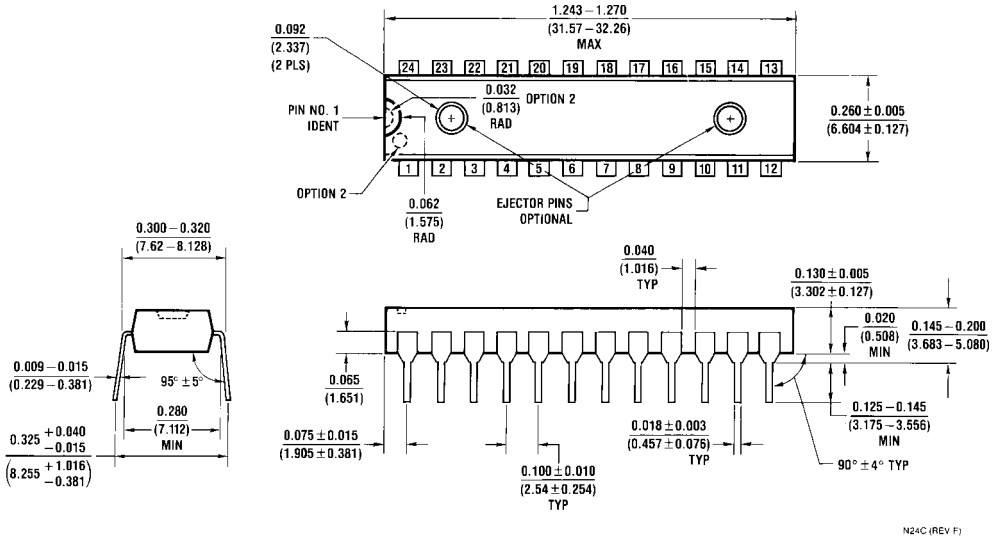
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.5		4.0		ns
$t_S(L)$	Data to CP	3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		2.0		
$t_H(L)$	Data to CP	1.0		1.0		
$t_S(H)$	Setup Time, HIGH or LOW	5.5		6.5		ns
$t_S(L)$	$\overline{PE}$ to CP	5.5		6.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	$\overline{PE}$ to CP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	6.0		6.5		ns
$t_S(L)$	$\overline{CET}$ or $\overline{CEP}$ to CP	8.0		9.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	$\overline{CET}$ or $\overline{CEP}$ to CP	0		0		
$t_W(H)$	Clock Pulse Width, HIGH or LOW	3.5		3.5		ns
$t_W(L)$		3.5		4.0		
$t_S(H)$	Setup Time, HIGH or LOW	8.0		9.5		ns
$t_S(L)$	U/$\overline{D}$ to CP	6.0		7.0		
$t_H(H)$	Hold Time, HIGH or LOW	0.0		0.0		ns
$t_H(L)$	U/$\overline{D}$ to CP	0.0		0.0		

Physical Dimensions inches (millimeters) unless otherwise noted



28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR TM

April 1988
Revised August 1999

74F27
Triple 3-Input NOR Gate

General Description

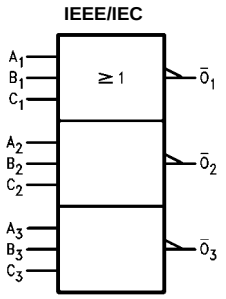
This device contains three independent gates, each of which performs the logic NOR function.

Ordering Code:

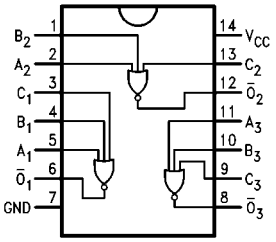
Order Number	Package Number	Package Description
74F27SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F27SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F27PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n, C_n	Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_n$	Data Outputs	50/33.3	–1 mA/20 mA

Function Table

Inputs			Output
A_n	B_n	C_n	$\overline{O}_n$
L	L	L	H
X	X	H	L
X	H	X	L
H	X	X	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

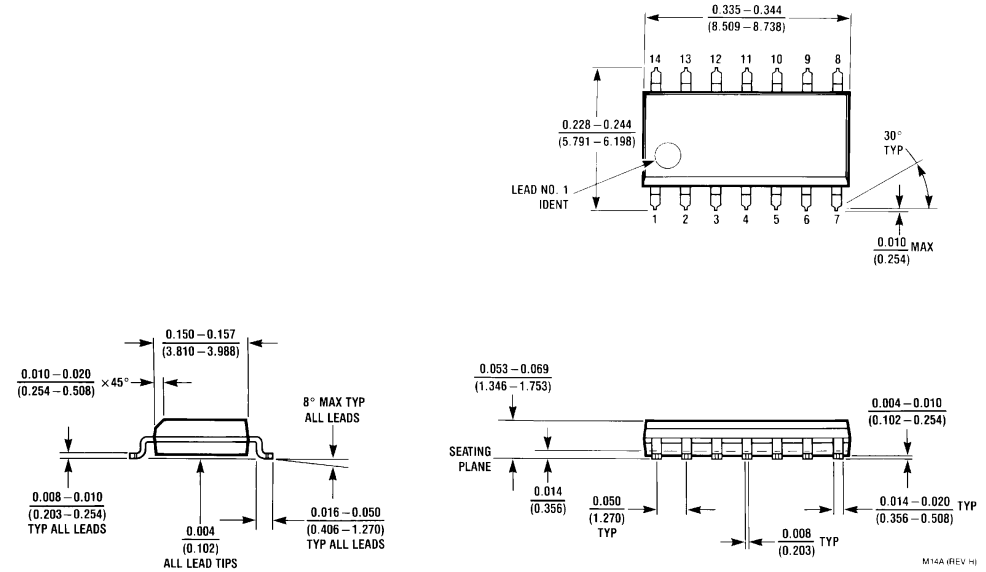
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
	Voltage							
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current				7.0	µA	Max	V_{IN} = 7.0V
	Breakdown Test							
I_{CEX}	Output HIGH				50	µA	Max	V_{OUT} = V_{CC}
	Leakage Current							
V_{ID}	Input Leakage		4.75			V	0.0	I_{ID} = 1.9 µA
	Test							All Other Pins Grounded
I_{OD}	Output Leakage				3.75	µA	0.0	V_{IOD} = 150 mV
	Circuit Current							All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			4.0	5.5	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			8.7	12.0	mA	Max	V_O = LOW

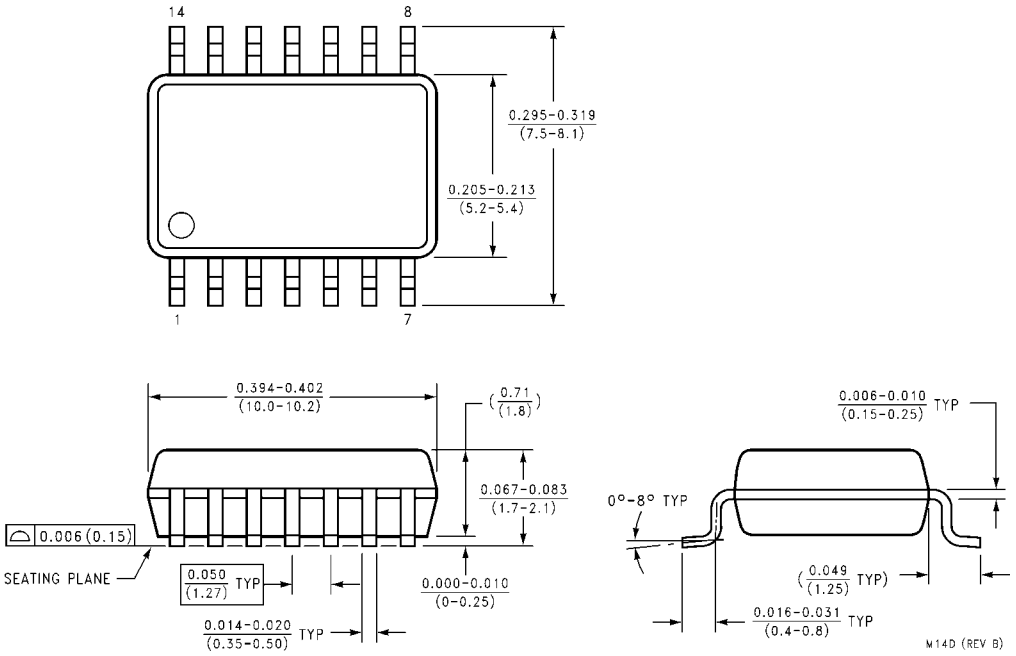
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.0	3.8	6.0	1.5	6.5	ns
t_{PHL}		1.0	2.6	4.0	1.0	4.5	

Physical Dimensions inches (millimeters) unless otherwise noted

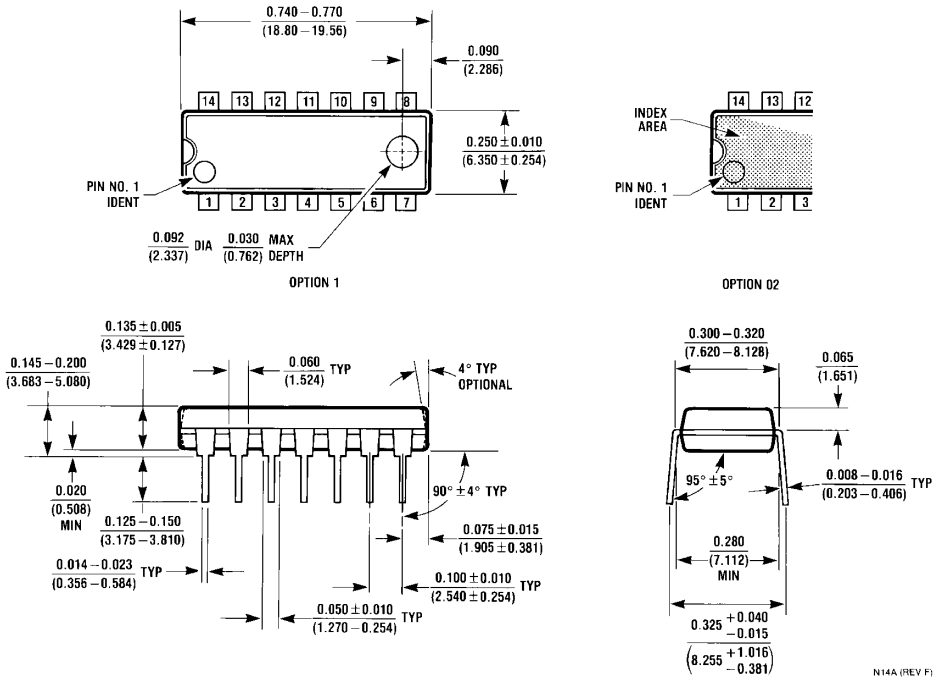


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F273
Octal D-Type Flip-Flop

General Description

The 74F273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

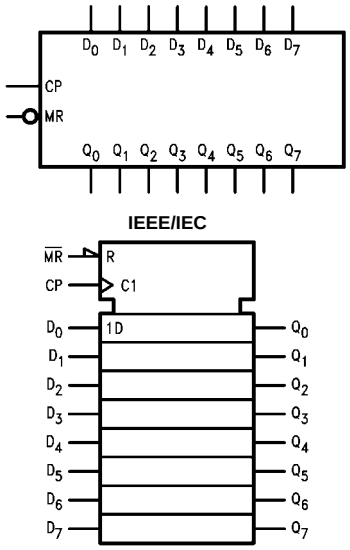
- Ideal buffer for MOS microprocessor or memory
- Eight edge-triggered D-type flip-flops
- Buffered common clock
- Buffered, asynchronous Master Reset
- See 74F377 for clock enable version
- See 74F373 for transparent latch version
- See 74F374 for 3-STATE version

Ordering Code:

Order Number	Package Number	Package Description
74F273SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F273PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

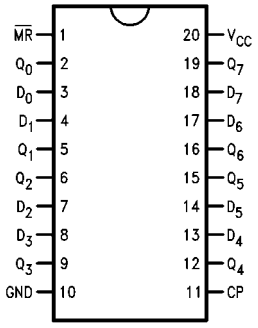
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Unit Loading/Fan Out

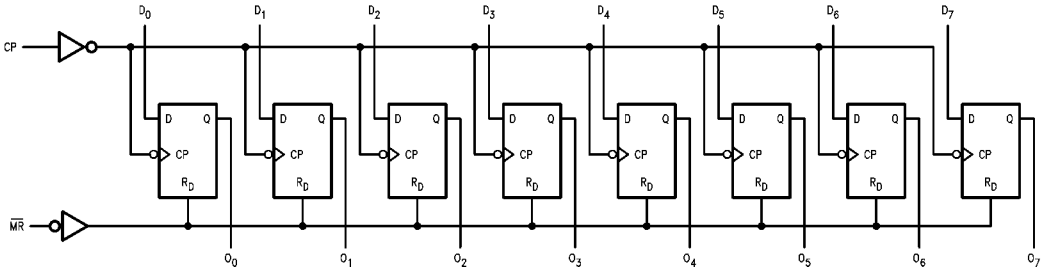
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{MR}$	Master Reset (Active LOW)	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_7	Data Outputs	50/33.3	–1 mA/20 mA

Mode Select-Function Table

Operating Mode	Inputs			Output
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load “1”	H	⌐	h	H
Load “0”	H	⌐	l	L

H = HIGH Voltage Level steady state
h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH clock transition
L = LOW Voltage Level steady state
l = LOW Voltage Level one setup time prior to the LOW-to-HIGH clock transition
X = Immaterial
⌐ = LOW-to-HIGH clock transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
		5% V_{CC}			0.5			
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH} I_{CCL}	Power Supply Current				44 56	mA	Max	CP = ⌐ D_n = $\overline{MR}$ = HIGH

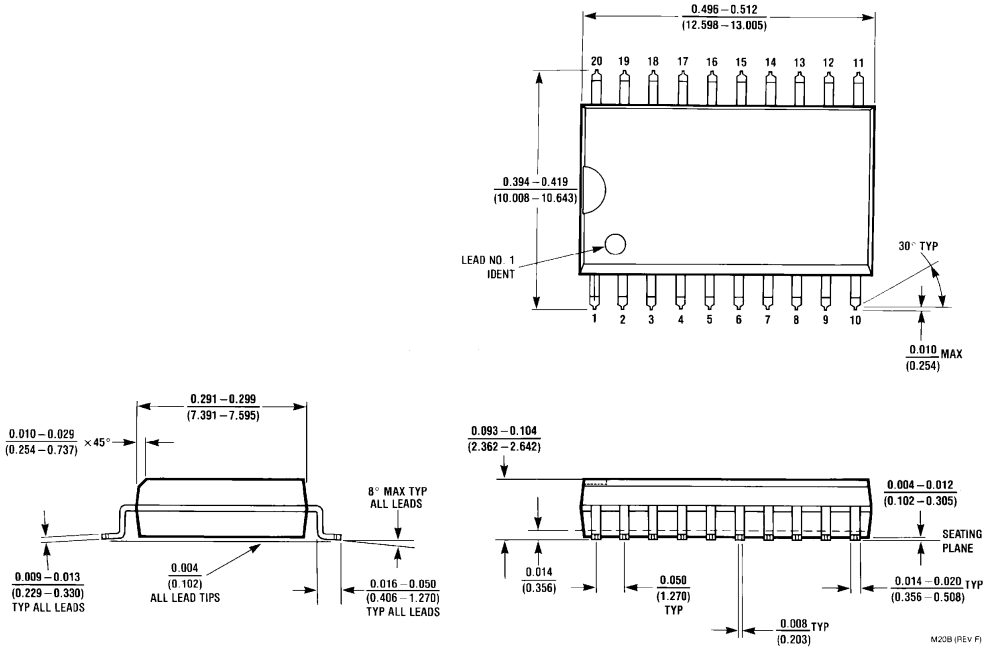
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	160			95		130		MHz
t_{PLH}	Propagation Delay	3.0		7.0	2.5	9.5	2.5	7.5	ns
t_{PHL}	Clock to Output	4.0		9.00	3.0	11.0	3.5	9.0	
t_{PLH}	Propagation Delay	4.5		9.5	3.0	11.0	4.0	10.0	ns
t_{PHL}	$\overline{MR}$ to Output								

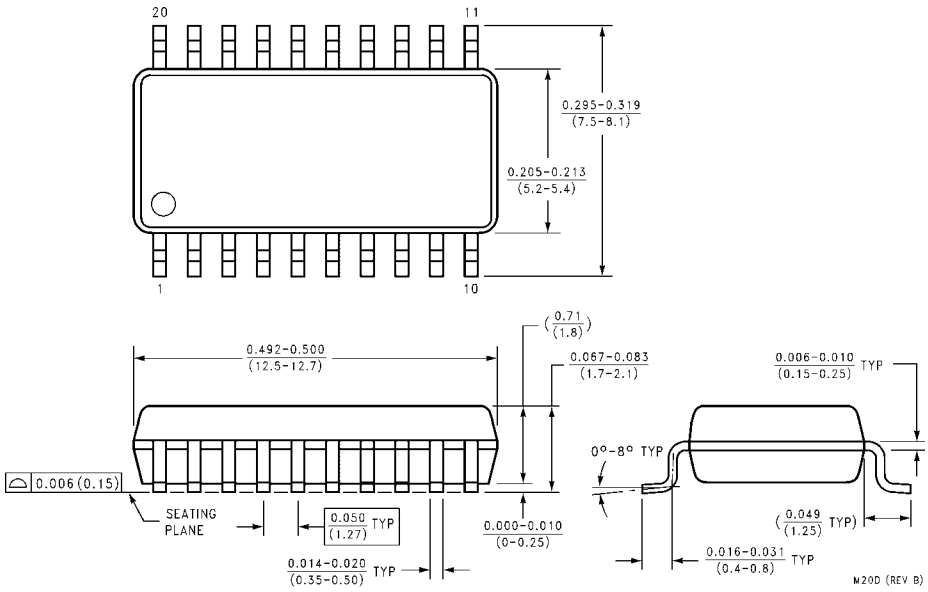
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = 5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.5		3.0		ns
$t_S(L)$	Data to CP	3.5		4.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	0.5		1.0		0.5		
$t_H(L)$	Data to CP	1.0		1.0		1.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	6.0		4.0		6.0		ns
$t_W(H)$	CP Pulse Width	6.0		5.0		6.0		ns
$t_W(L)$	HIGH or LOW	6.0		5.0		6.0		
t_{REC}	Recovery Time, $\overline{MR}$ to CP	3.0		4.5		3.5		ns

Physical Dimensions inches (millimeters) unless otherwise noted

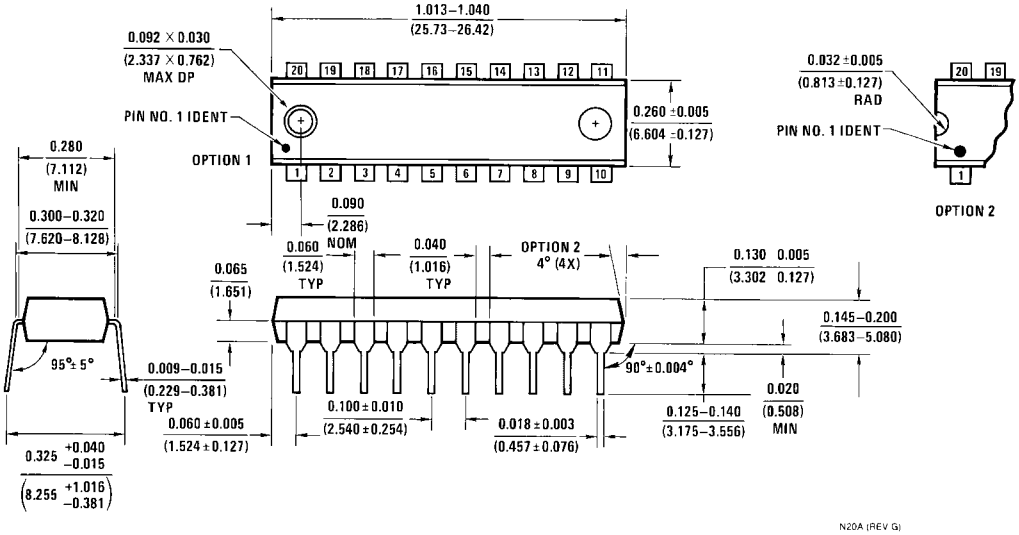


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F280
9-Bit Parity Generator/Checker

General Description

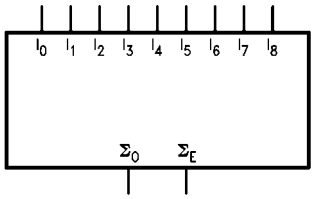
The F280 is a high-speed parity generator/checker that accepts nine bits of input data and detects whether an even or an odd number of these inputs is HIGH. If an even number of inputs is HIGH, the Sum Even output is HIGH. If an odd number is HIGH, the Sum Even output is LOW. The Sum Odd output is the complement of the Sum Even output.

Ordering Code:

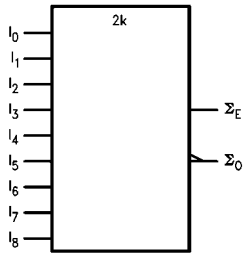
Order Number	Package Number	Package Description
74F280SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F280SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F280PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

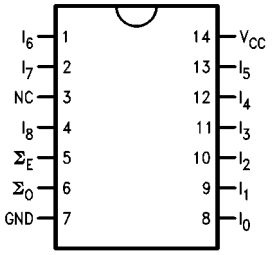
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

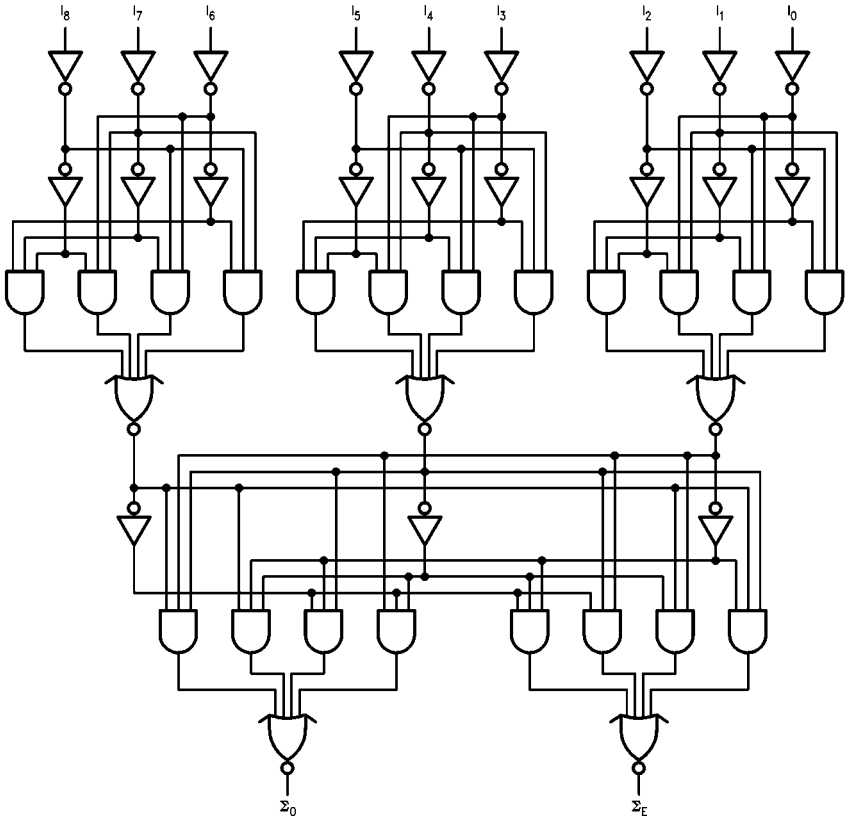
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_0–I_8	Data Inputs	1.0/1.0	20 μA/–0.6 mA
Σ_O	Odd Parity Output	50/33.3	–1 mA/20 mA
Σ_E	Even Parity Output	50/33.3	–1 mA/20 mA

Truth Table

Number of HIGH Inputs I_0–I_8	Outputs	
	Σ Even	Σ Odd
0, 2, 4, 6, 8	H	L
1, 3, 5, 7, 9	L	H

H = HIGH Voltage Level
L = LOW Voltage Level

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

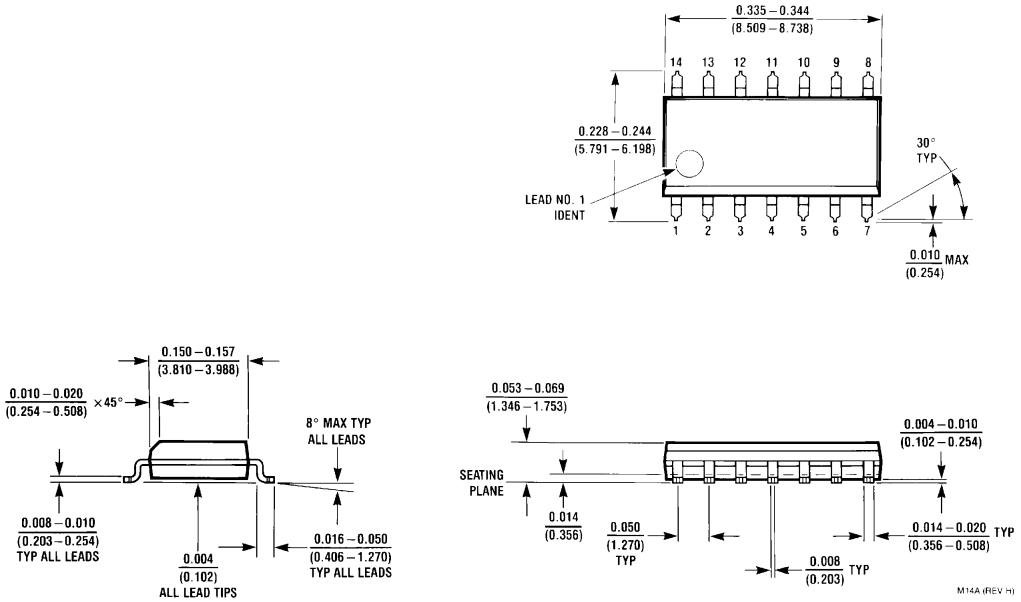
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			25	38	mA	Max	V_O = HIGH

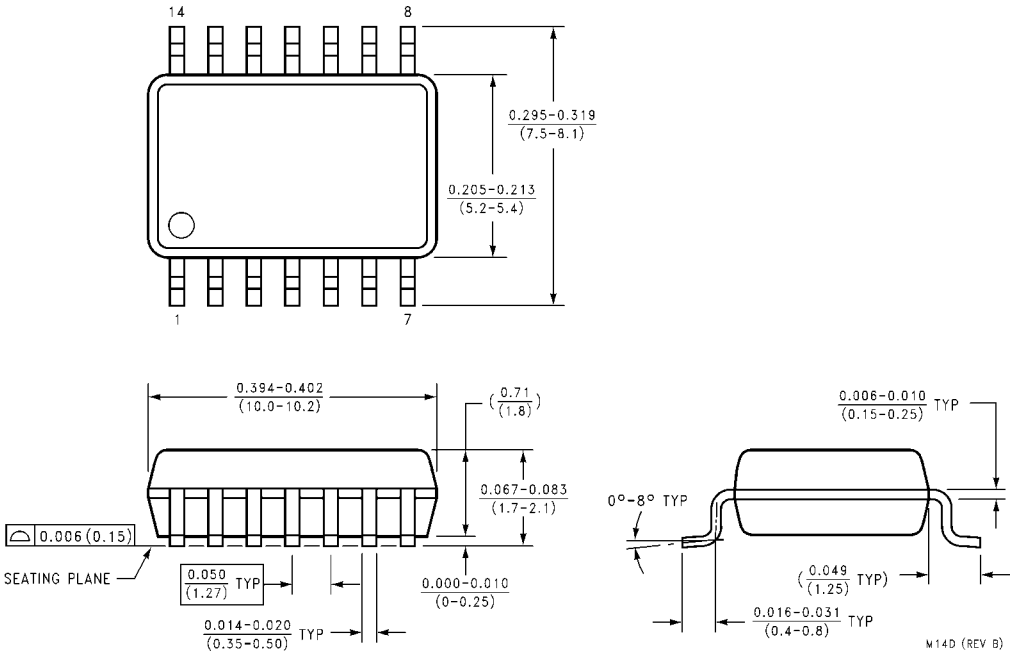
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = 5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = 5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	6.5	10.0	15.0	6.5	20.0	6.5	16.0	ns
t_{PHL}	I_n to Σ_E	6.5	11.0	16.0	6.5	21.0	6.5	17.0	
t_{PLH}	Propagation Delay	6.0	10.0	15.0	5.0	20.0	6.0	16.0	ns
t_{PHL}	I_n to Σ_O	6.5	11.0	16.0	6.5	21.0	6.5	17.0	

Physical Dimensions inches (millimeters) unless otherwise noted

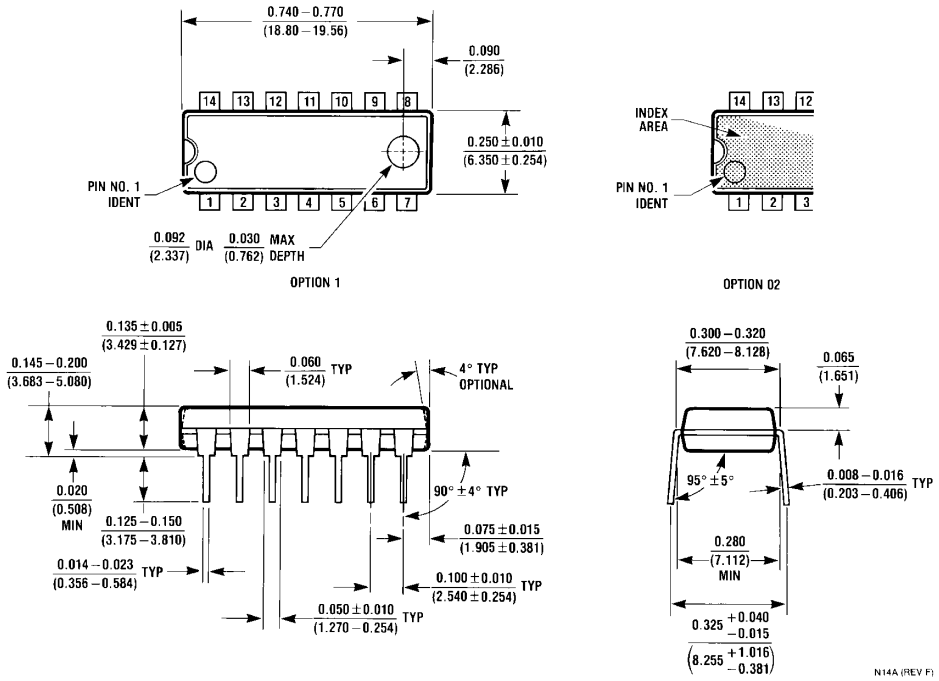


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F283
4-Bit Binary Full Adder with Fast Carry

General Description

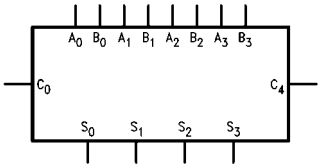
The 74F283 high-speed 4-bit binary full adder with internal carry lookahead accepts two 4-bit binary words (A_0–A_3, B_0–B_3) and a Carry input (C_0). It generates the binary Sum outputs (S_0–S_3) and the Carry output (C_4) from the most significant bit. The 74F283 will operate with either active HIGH or active LOW operands (positive or negative logic).

Ordering Code:

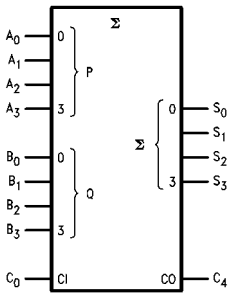
Order Number	Package Number	Package Description
74F283SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F283SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F283PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

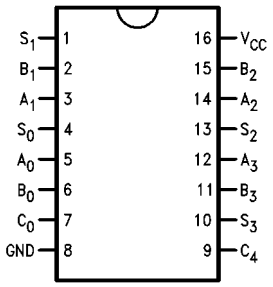
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	A Operand Inputs	1.0/2.0	20 µA/–1.2 mA
B_0–B_3	B Operand Inputs	1.0/2.0	20 µA/–1.2 mA
C_0	Carry Input	1.0/1.0	20 µA/–0.6 mA
S_0–S_3	Sum Outputs	50/33.3	–1 mA/20 mA
C_4	Carry Output	50/33.3	–1 mA/20 mA

Functional Description

The 74F283 adds two 4-bit binary words (A plus B) plus the incoming Carry (C_0). The binary sum appears on the Sum (S_0–S_3) and outgoing carry (C_4) outputs. The binary weight of the various inputs and outputs is indicated by the subscript numbers, representing powers of two.

$$2^0 (A_0 + B_0 + C_0) + 2^1 (A_1 + B_1)$$
$$+ 2^2 (A_2 + B_2) + 2^3 (A_3 + B_3)$$
$$= S_0 + 2S_1 + 4S_2 + 8S_3 + 16C_4$$

Where (+) = plus

Interchanging inputs of equal weight does not affect the operation. Thus C_0, A_0, B_0 can be arbitrarily assigned to pins 5, 6 and 7 for DIPS, and 7, 8 and 9 for chip carrier packages. Due to the symmetry of the binary add function, the 74F283 can be used either with all inputs and outputs active HIGH (positive logic) or with all inputs and outputs active LOW (negative logic). See Figure 1. Note that if C_0 is not used it must be tied LOW for active HIGH logic or tied HIGH for active LOW logic.

Due to pin limitations, the intermediate carries of the 74F283 are not brought out for use as inputs or outputs. However, other means can be used to effectively insert a carry into, or bring a carry out from, an intermediate stage. Figure 2 shows how to make a 3-bit adder. Tying the operand inputs of the fourth adder (A_3, B_3) LOW makes S_3 dependent only on, and equal to, the carry from the third adder. Using somewhat the same principle, Figure 3 shows a way of dividing the 74F283 into a 2-bit and a 1-bit adder. The third stage adder (A_2, B_2, S_2) is used merely as a means of getting a carry (C_{10}) signal into the fourth stage (via A_2 and B_2) and bringing out the carry from the second stage on S_2. Note that as long as A_2 and B_2 are the same, whether HIGH or LOW, they do not influence S_2. Similarly, when A_2 and B_2 are the same the carry into the third stage does not influence the carry out of the third stage. Figure 4 shows a method of implementing a 5-input encoder, where the inputs are equally weighted. The outputs S_0, S_1 and S_2 present a binary number equal to the number of inputs I_1–I_5 that are true. Figure 5 shows one method of implementing a 5-input majority gate. When three or more of the inputs I_1–I_5 are true, the output M_5 is true.

	C_0	A_0	A_1	A_2	A_3	B_0	B_1	B_2	B_3	S_0	S_1	S_2	S_3	C_4
Logic Levels	L	L	H	L	H	H	L	L	H	H	H	L	L	H
Active HIGH	0	0	1	0	1	1	0	0	1	1	1	0	0	1
Active LOW	1	1	0	1	0	0	1	1	0	0	0	1	1	0

Active HIGH: 0 + 10 + 9 = 3 + 16 Active LOW: 1 + 5 + 6 = 12 + 0

FIGURE 1. Active HIGH versus Active LOW Interpretation

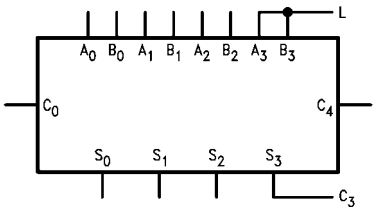


FIGURE 2. 3-Bit Adder

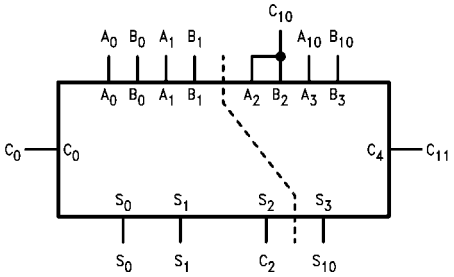


FIGURE 3. 2-Bit and 1-Bit Adders

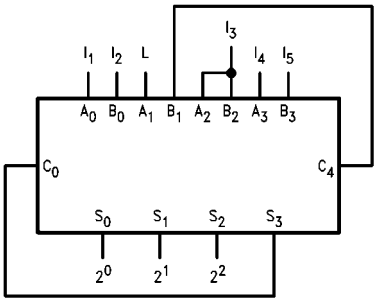


FIGURE 4. 5-Input Encoder

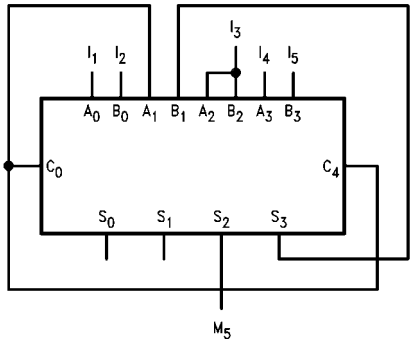
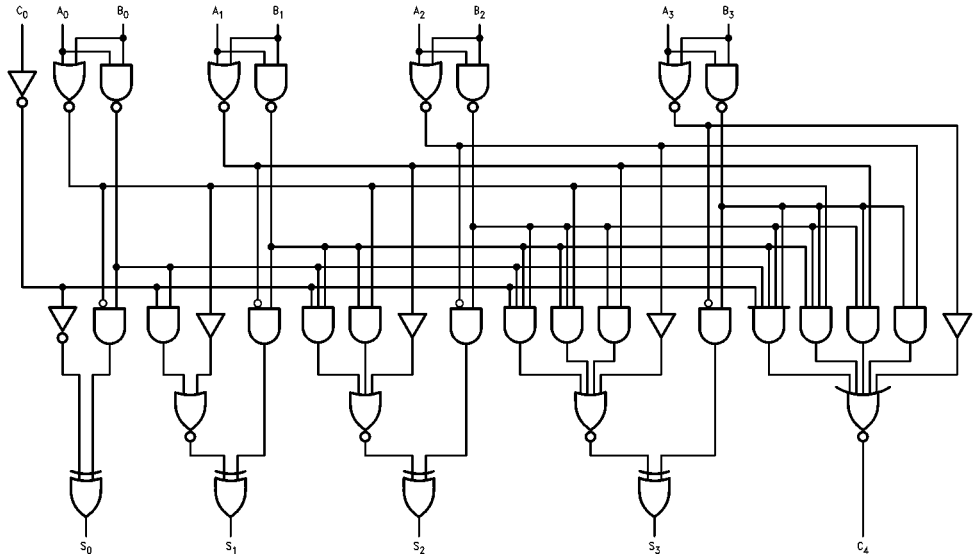


FIGURE 5. 5-Input Majority Gate

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

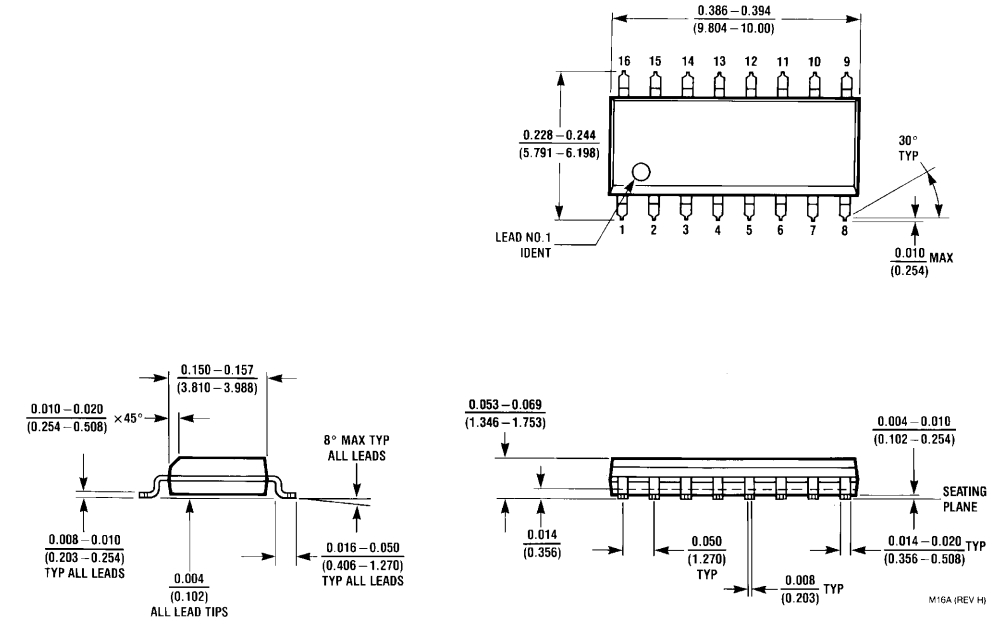
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (C_O)
					−1.2			V_{IN} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			36	55	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			36	55	mA	Max	V_O = LOW

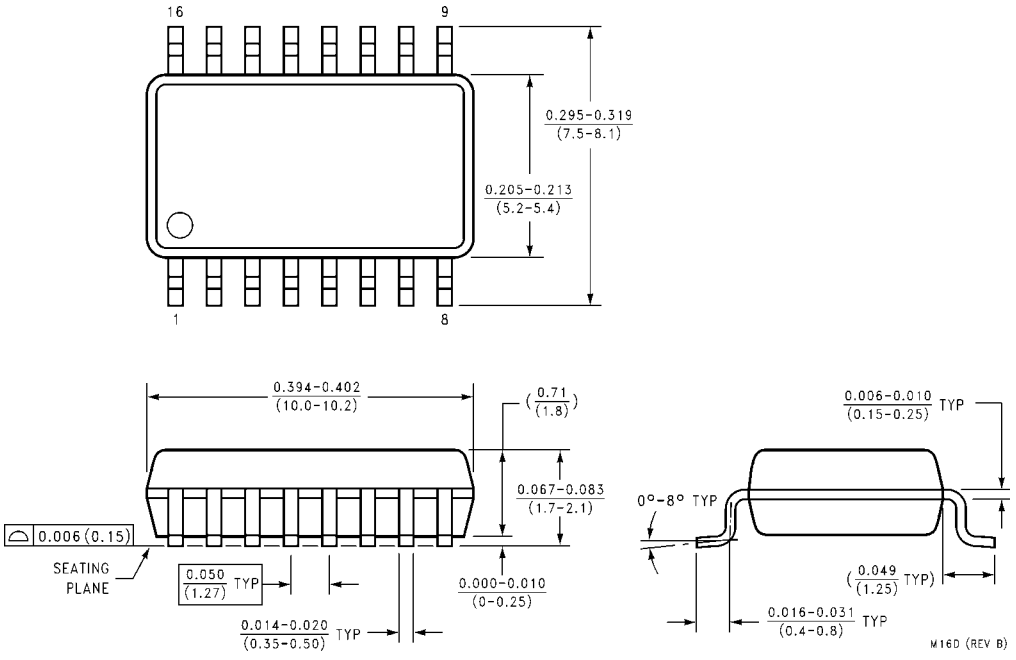
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = 5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = 5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.5	7.0	9.5	3.5	14.0	3.5	11.0	ns
t_{PHL}	C_0 to S_n	3.0	7.0	9.5	3.0	14.0	3.0	11.0	
t_{PLH}	Propagation Delay	3.0	7.0	9.5	3.0	17.0	3.0	13.0	ns
t_{PHL}	A_n or B_n to S_n	3.0	7.0	9.5	3.0	14.0	3.0	11.5	
t_{PLH}	Propagation Delay	3.0	5.7	7.5	3.0	10.5	3.0	8.5	ns
t_{PHL}	C_0 to C_4	3.0	5.4	7.0	2.5	10.0	3.0	8.0	
t_{PLH}	Propagation Delay	3.0	5.7	7.5	3.0	10.5	3.0	8.5	ns
t_{PHL}	A_n or B_n to C_4	2.5	5.3	7.0	2.5	10.0	2.5	8.0	

Physical Dimensions inches (millimeters) unless otherwise noted

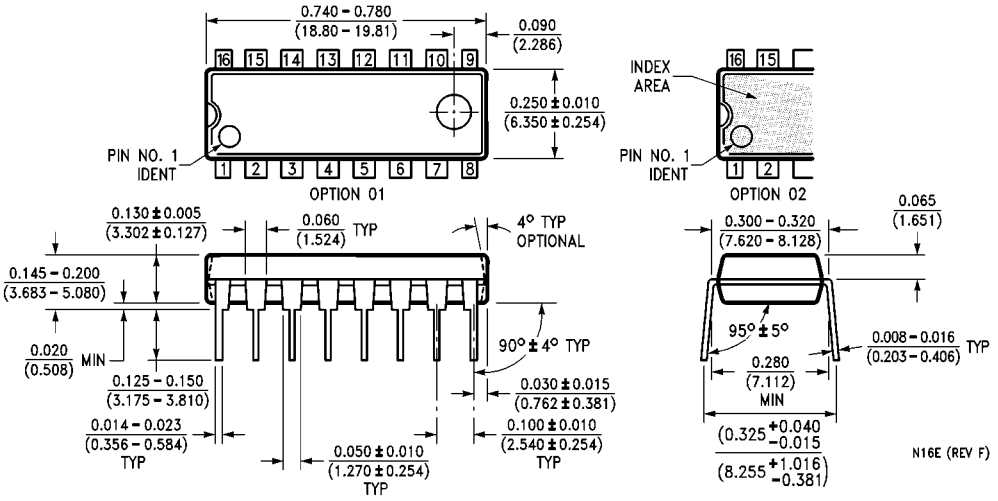


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F299
Octal Universal Shift/Storage Register with Common Parallel I/O Pins

General Description

The 74F299 is an 8-bit universal shift/storage register with 3-STATE outputs. Four modes of operation are possible: hold (store), shift left, shift right and load data. The parallel load inputs and flip-flop outputs are multiplexed to reduce the total number of package pins. Additional outputs, Q_0–Q_7, are provided to allow easy serial cascading. A separate active LOW Master Reset is used to reset the register.

Features

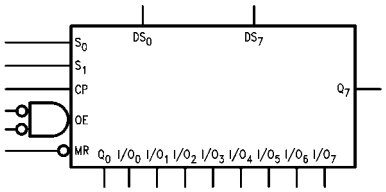
- Common parallel I/O for reduced pin count
- Additional serial inputs and outputs for expansion
- Four operating modes: shift left, shift right, load and store
- 3-STATE outputs for bus-oriented applications
- Guaranteed 4000V minimum ESD protection

Ordering Code:

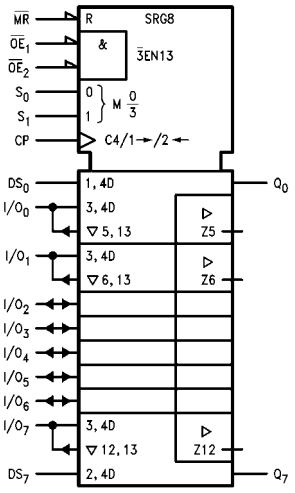
Order Number	Package Number	Package Description
74F299SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F299SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F299PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

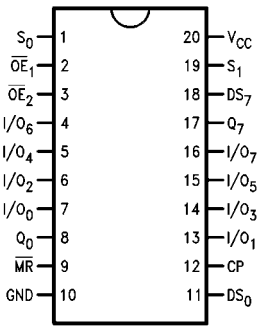
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
DS_0	Serial Data Input for Right Shift	1.0/1.0	20 µA/–0.6 mA
DS_7	Serial Data Input for Left Shift	1.0/1.0	20 µA/–0.6 mA
S_0, S_1	Mode Select Inputs	1.0/2.0	20 µA/–1.2 mA
$\overline{MR}$	Asynchronous Master Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs (Active LOW)	1.0/1.0	20 µA/–0.6 mA
I/O_0–I/O_7	Parallel Data Inputs or	3.5/1.083	70 µA/–0.65 mA
	3-STATE Parallel Outputs	150/40(33.3)	–3 mA/24 mA (20 mA)
Q_0, Q_7	Serial Outputs	50/33.3	–1 mA/20 mA

Functional Description

The 74F299 contains eight edge-triggered D-type flip-flops and the interstage logic necessary to perform synchronous shift left, shift right, parallel load and hold operations. The type of operation is determined by S_0 and S_1, as shown in the Mode Select Table. All flip-flop outputs are brought out through 3-STATE buffers to separate I/O pins that also serve as data inputs in the parallel load mode. Q_0 and Q_7 are also brought out on other pins for expansion in serial shifting of longer words.

A LOW signal on $\overline{MR}$ overrides the Select and CP inputs and resets the flip-flops. All other state changes are initiated by the rising edge of the clock. Inputs can change when the clock is in either state provided only that the recommended setup and hold times, relative to the rising edge of CP, are observed.

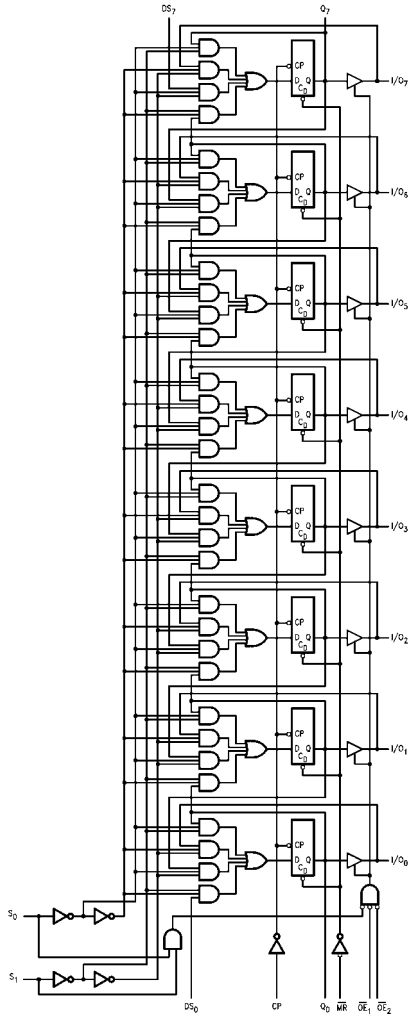
A HIGH signal on either $\overline{OE}_1$ or $\overline{OE}_2$ disables the 3-STATE buffers and puts the I/O pins in the high impedance state. In this condition the shift, hold, load and reset operations can still occur. The 3-STATE outputs are also disabled by HIGH signals on both S_0 and S_1 in preparation for a parallel load operation.

Mode Select Table

Inputs				Response
$\overline{MR}$	S_1	S_0	CP	
L	X	X	X	Asynchronous Reset; Q_0–Q_7 = LOW
H	H	H	↗	Parallel Load; $I/O_n \rightarrow Q_n$
H	L	H	↗	Shift Right; $DS_0 \rightarrow Q_0$, $Q_0 \rightarrow Q_1$, etc.
H	H	L	↗	Shift Left; $DS_7 \rightarrow Q_7$, $Q_7 \rightarrow Q_6$, etc.
H	L	L	X	Hold

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↗ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
ESD Last Passing Voltage (Min)	4000V
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	
Current Applied to Output	−0.5V to +5.5V
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA (Q_0, Q_7, I/O_n)
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA (I/O_n)
		5% V_{CC}	2.7					I_{OH} = −1 mA (Q_0, Q_7, I/O_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (I/O_n)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA (Q_0, Q_7)
	Voltage	10% V_{CC}			0.5			I_{OL} = 24 mA (I/O_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V (CP, DS_0, DS_7, S_0, S_1, $\overline{MR}$, $\overline{OE_1}$, $\overline{OE_2}$)
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (CP, DS_0, DS_7, S_0, S_1, $\overline{MR}$, $\overline{OE_1}$, $\overline{OE_2}$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)				0.5	mA	Max	V_{IN} = 5.5V (I/O_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (CP, DS_0, DS_7, $\overline{MR}$, $\overline{OE_1}$, $\overline{OE_2}$)
					−1.2			V_{IN} = 0.5V (S_0, S_1)
I_{IH}+ I_{OZH}	Output Leakage Current				70	µA	Max	$V_{I/O}$ = 2.7V (I/O_n)
I_{IL}+ I_{OZL}	Output Leakage Current				−650	µA	Max	$V_{I/O}$ = 0.5V (I/O_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			68	95	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			68	95	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			68	95	mA	Max	V_O = HIGH Z

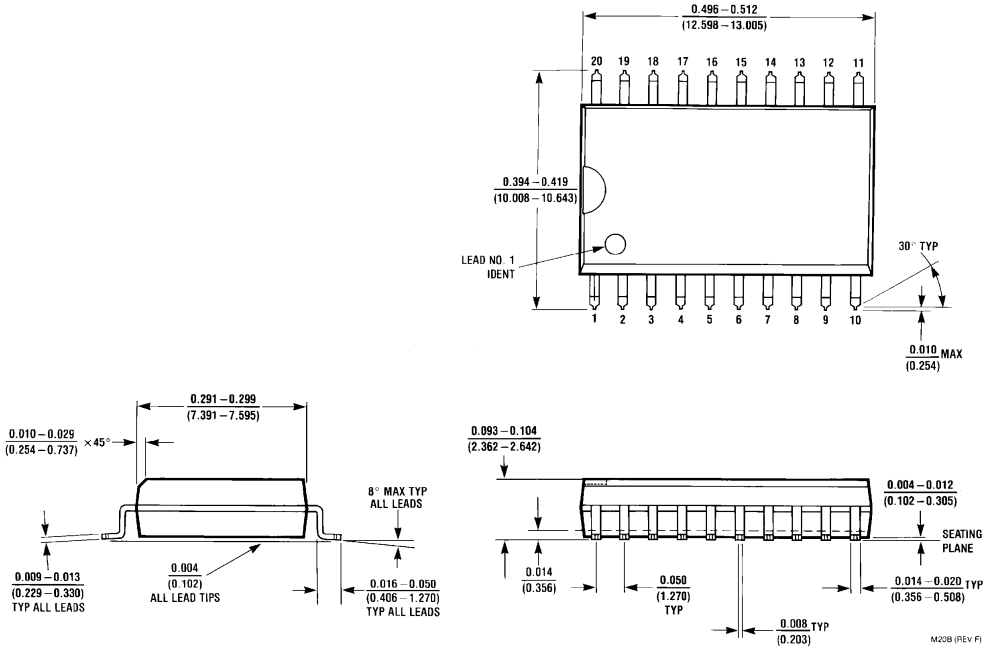
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		$T_A = 0$ to $+70°C$, $V_{CC} = 5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Input Frequency	70	100		85		70		MHz
t_{PLH}	Propagation Delay	4.0	7.0	8.0	4.0	9.0	4.0	8.5	ns
t_{PHL}	CP to Q_0 or Q_7	4.5	6.5	8.0	4.5	9.5	4.5	8.5	
t_{PLH}	Propagation Delay	3.5	7.0	9.0	3.5	10.0	3.5	10.0	
t_{PHL}	CP to I/O_n	4.0	8.5	9.0	4.0	11.0	4.0	10.0	
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_0 or Q_7	5.5	7.5	9.5	5.5	12.5	5.5	10.5	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to I/O_n	5.5	11.0	10.0	5.5	12.0	5.5	10.5	ns
t_{PZH}	Output Enable Time	3.5	6.0	8.0	3.0	9.5	3.5	9.0	ns
t_{PZL}	$\overline{OE}$ to I/O_n	4.0	7.0	10.0	4.0	13.0	4.0	11.0	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	1.5	7.0	2.0	7.0	
t_{PLZ}	$\overline{OE}$ to I/O_n	1.0	4.0	5.5	1.0	6.5	1.0	6.5	
t_{PZH}	Output Enable Time	3.5		9.0	3.0	10.5	3.5	10.0	ns
t_{PZL}	S_n to I/O_n	4.0		10.0	4.0	13.0	4.0	11.0	
t_{PHZ}	Output Disable Time	2.5		6.0	1.5	7.0	2.5	7.0	ns
t_{PLZ}	S_n to I/O_n	1.5		5.5	1.0	6.5	1.5	6.5	

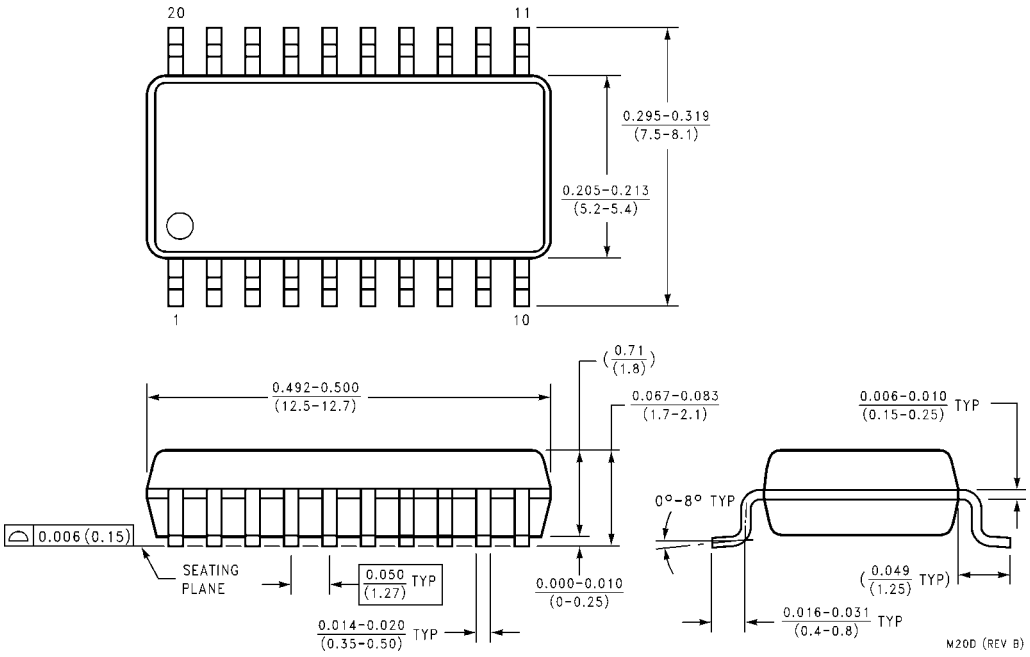
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = 5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = 5.0V$		$T_A = 0$ to $+70°C$, $V_{CC} = 5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	8.5		10.0		8.5		ns
$t_S(L)$	S_0 or S_1 to CP	8.5		7.5		8.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	S_0 or S_1 to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	5.0		5.0		5.0		ns
$t_S(L)$	I/O_n, DS_0 or DS_7 to CP	5.0		5.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	I/O_n, DS_0 or DS_7 to CP	2.0		2.0		2.0		
$t_W(H)$	CP Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	5.0		6.0		5.0		ns
t_{REC}	Recovery Time, $\overline{MR}$ to CP	7.0		12.0		7.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

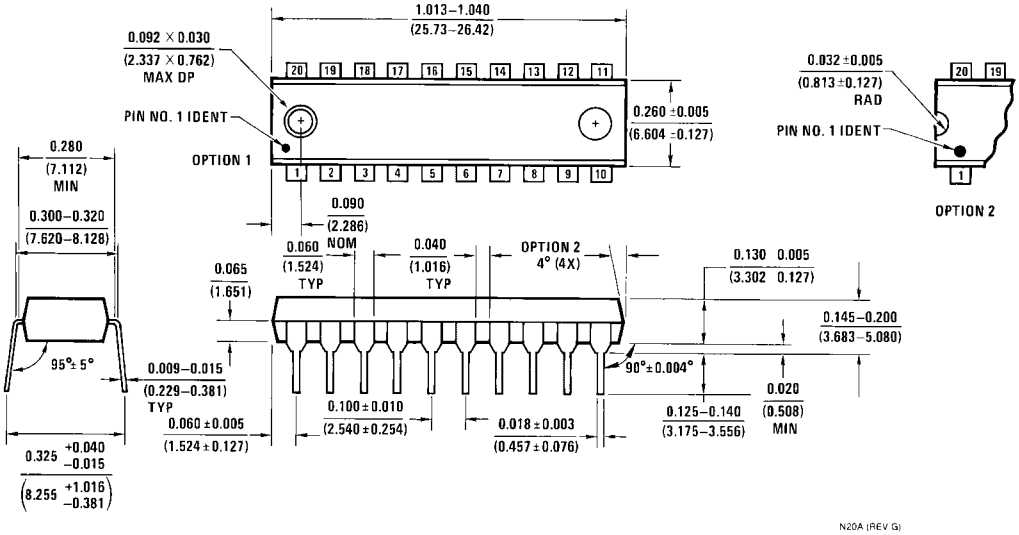


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number MD20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F30
8-Input NAND Gate

General Description

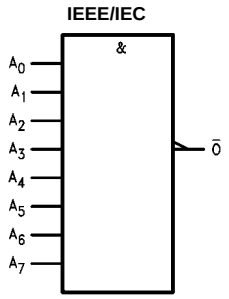
This device contains a single gate, which performs the logic NAND function.

Ordering Code:

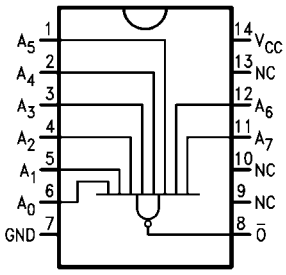
Order Number	Package Number	Package Description
74F30SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F30SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F30PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{O}$	Output	50/33.3	–1 mA/20 mA

Function Table

Inputs								Output
A_0	A_1	A_2	A_3	A_4	A_5	A_6	A_7	$\overline{O}$
L	X	X	X	X	X	X	X	H
X	L	X	X	X	X	X	X	H
X	X	L	X	X	X	X	X	H
X	X	X	L	X	X	X	X	H
X	X	X	X	L	X	X	X	H
X	X	X	X	X	L	X	X	H
X	X	X	X	X	X	L	X	H
X	X	X	X	X	X	X	L	H
H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

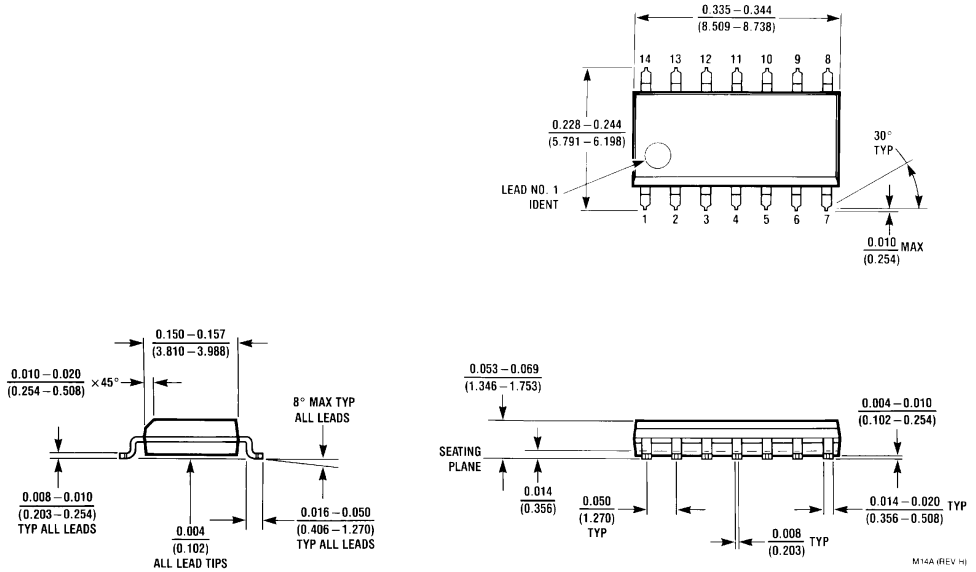
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			0.5	1.5	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current				4.5	mA	Max	V_O = LOW

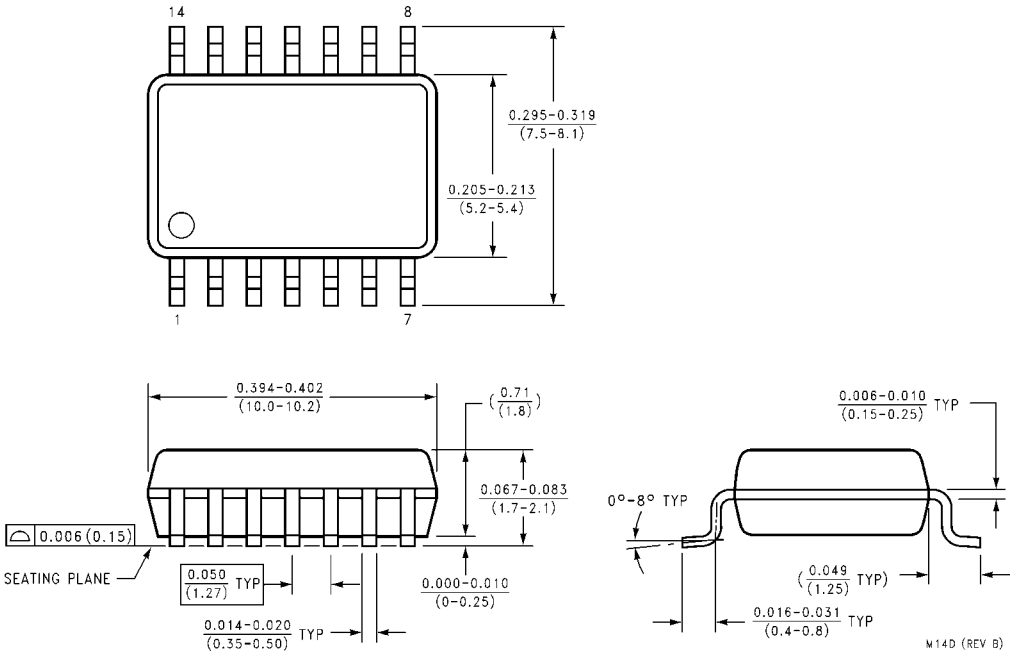
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	3.7	5.0	1.0	5.5	ns
t_{PHL}	A_n to $\overline{O}$	1.5	2.8	5.0	1.5	5.5	

Physical Dimensions inches (millimeters) unless otherwise noted

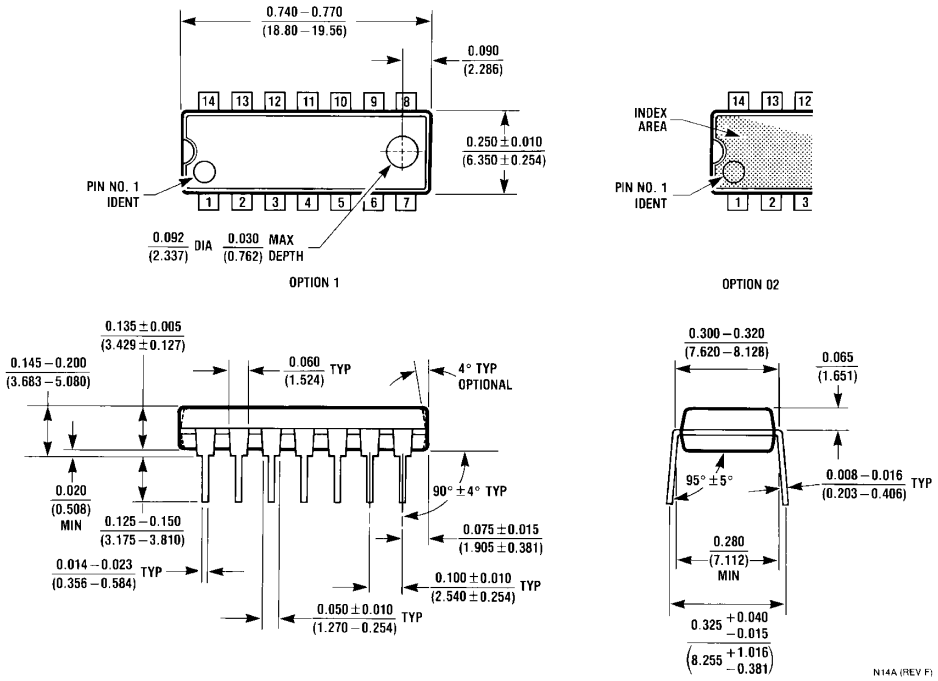


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F32
Quad 2-Input OR Gate

General Description

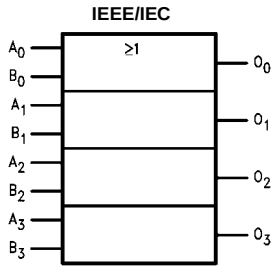
This device contains four independent gates, each of which performs the logic OR function.

Ordering Code:

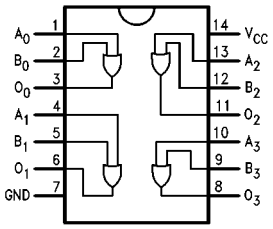
Order Number	Package Number	Package Description
74F32SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F32PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/1.0	20 μA/–0.6 mA
O_n	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

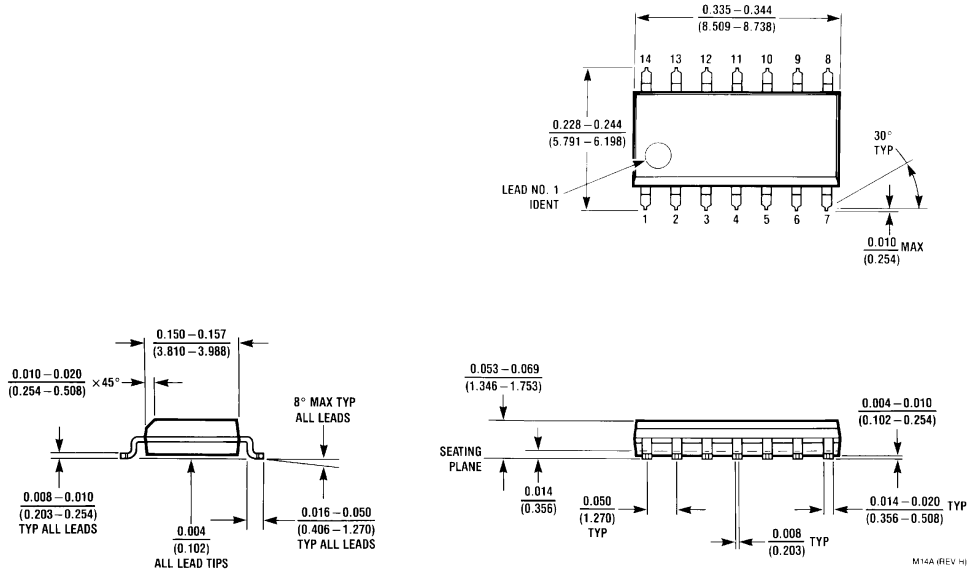
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			6.1	9.2	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			10.3	15.5	mA	Max	V_O = LOW

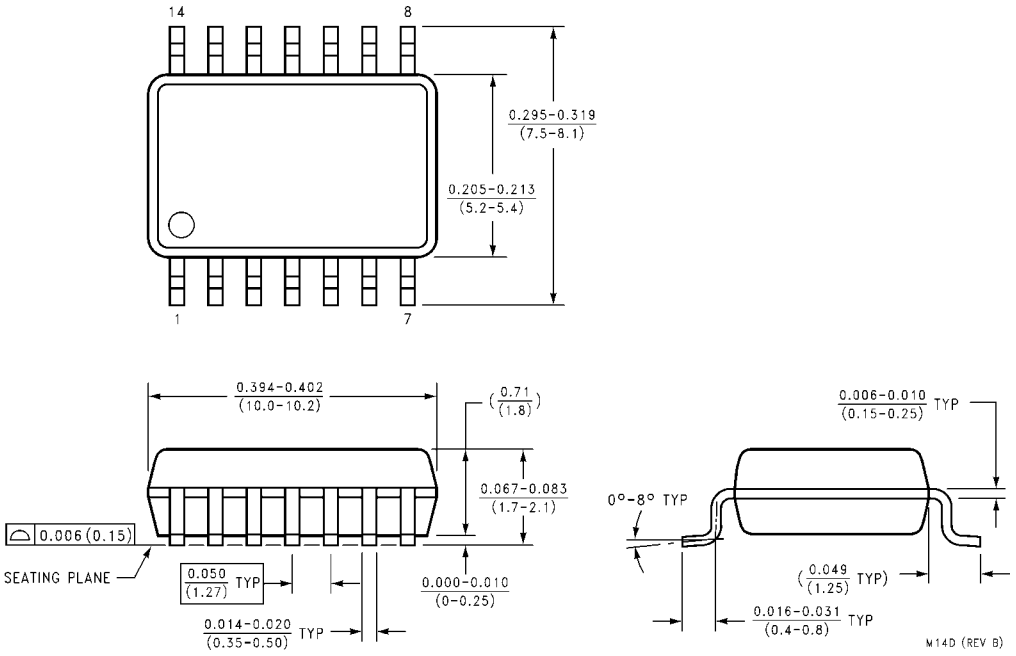
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	4.2	5.6	3.0	7.5	3.0	6.6	ns
t_{PHL}	A_n, B_n to O_n	3.0	4.0	5.3	2.5	7.5	3.0	6.3	

Physical Dimensions inches (millimeters) unless otherwise noted

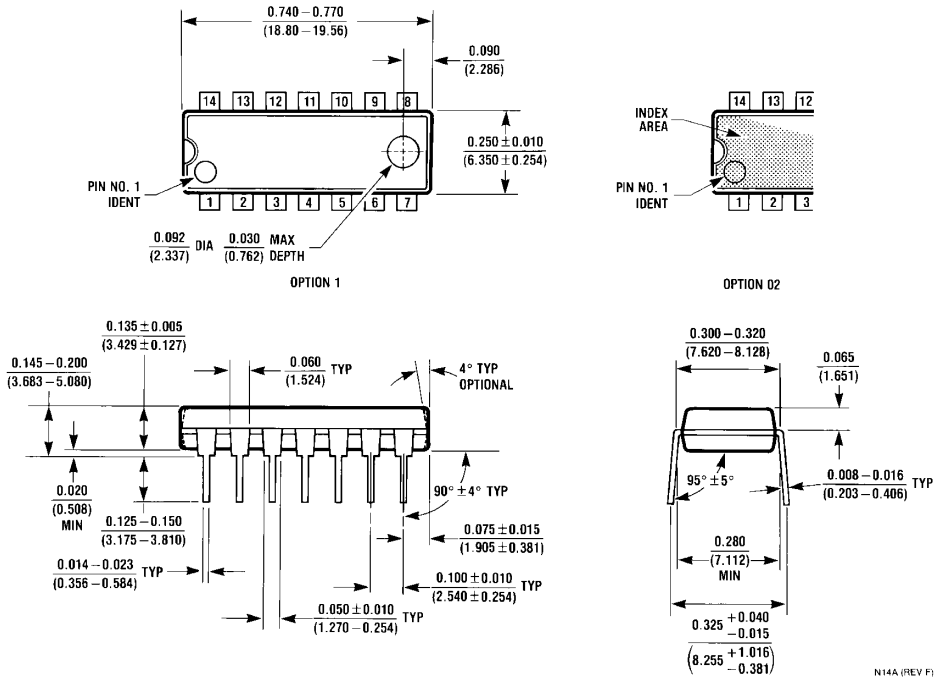


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR TM

April 1988
Revised April 1999

74F322
Octal Serial/Parallel Register with Sign Extend

General Description

The 74F322 is an 8-bit shift register with provision for either serial or parallel loading and with 3-STATE parallel outputs plus a bi-state serial output. Parallel data inputs and parallel outputs are multiplexed to minimize pin count. State changes are initiated by the rising edge of the clock. Four synchronous modes of operation are possible: hold (store), shift right with serial entry, shift right with sign extend and parallel load. An asynchronous Master Reset ($\overline{MR}$) input overrides clocked operation and clears the register.

Features

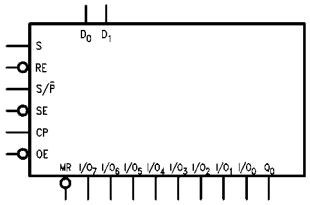
- Multiplexed parallel I/O ports
- Separate serial input and output
- Sign extend function
- 3-STATE outputs for bus applications

Ordering Code:

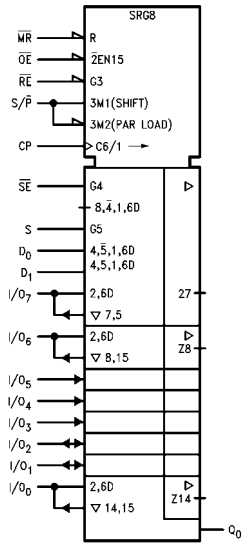
Order Number	Package Number	Package Description
74F322PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

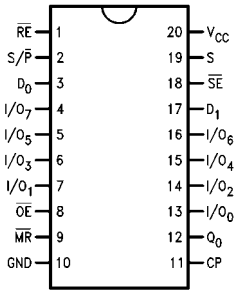
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{RE}$	Register Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$S/\overline{P}$	Serial (HIGH) or Parallel (LOW) Mode Control Input	1.0/1.0	20 µA/–0.6 mA
$\overline{SE}$	Sign Extend Input (Active LOW)	1.0/3.0	20 µA/–1.8 mA
S	Serial Data Select Input	1.0/2.0	20 µA/–1.2 mA
D_0, D_1	Serial Data Inputs	1.0/1.0	20 µA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{MR}$	Asynchronous Master Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
Q_0	Bi-State Serial Output	50/33.3	–1 mA/–20 mA
I/O_0–I/O_7	Multiplexed Parallel Data Inputs or	3.5/1.083	70 µA/–0.65 mA
	3-STATE Parallel Data Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

The 74F322 contains eight D-type edge triggered flip-flops and the interstage gating required to perform right shift and the intrastage gating necessary for hold and synchronous parallel load operations. A LOW signal on $\overline{RE}$ enables shifting or parallel loading, while a HIGH signal enables the hold mode. A HIGH signal on $S/\overline{P}$ enables shift right, while a LOW signal disables the 3-STATE output buffers and enables parallel loading. In the shift right mode a HIGH signal on $\overline{SE}$ enables serial entry from either D_0 or D_1, as determined by the S input. A LOW signal on $\overline{SE}$ enables shift right but Q_7 reloads its contents, thus performing the sign extend function required for the 74F384 Twos Complement Multiplier. A HIGH signal on $\overline{OE}$ disables the 3-STATE output buffers, regardless of the other control inputs. In this condition the shifting and loading operations can still be performed.

Mode Select Table

Mode	Inputs							Outputs								Q_0
	$\overline{MR}$	$\overline{RE}$	$S/\overline{P}$	$\overline{SE}$	S	$\overline{OE}$ (Note 1)	CP	I/O_7	I/O_6	I/O_5	I/O_4	I/O_3	I/O_2	I/O_1	I/O_0	
Clear	L	X	X	X	X	L	X	L	L	L	L	L	L	L	L	L
	L	X	X	X	X	H	X	Z	Z	Z	Z	Z	Z	Z	Z	L
Parallel Load	H	L	L	X	X	X	⌐	I_7	I_6	I_5	I_4	I_3	I_2	I_1	I_0	I_0
Shift Right	H	L	H	H	L	L	⌐	D_0	O_7	O_6	O_5	O_4	O_3	O_2	O_1	O_1
	H	L	H	H	H	L	⌐	D_1	O_7	O_6	O_5	O_4	O_3	O_2	O_1	O_1
Sign Extend	H	L	H	L	X	L	⌐	O_7	O_7	O_6	O_5	O_4	O_3	O_2	O_1	O_1
Hold	H	H	X	X	X	L	⌐	NC	NC	NC	NC	NC	NC	NC	NC	NC

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance Output State
⌐ = LOW-to-HIGH Transition
NC = No Change

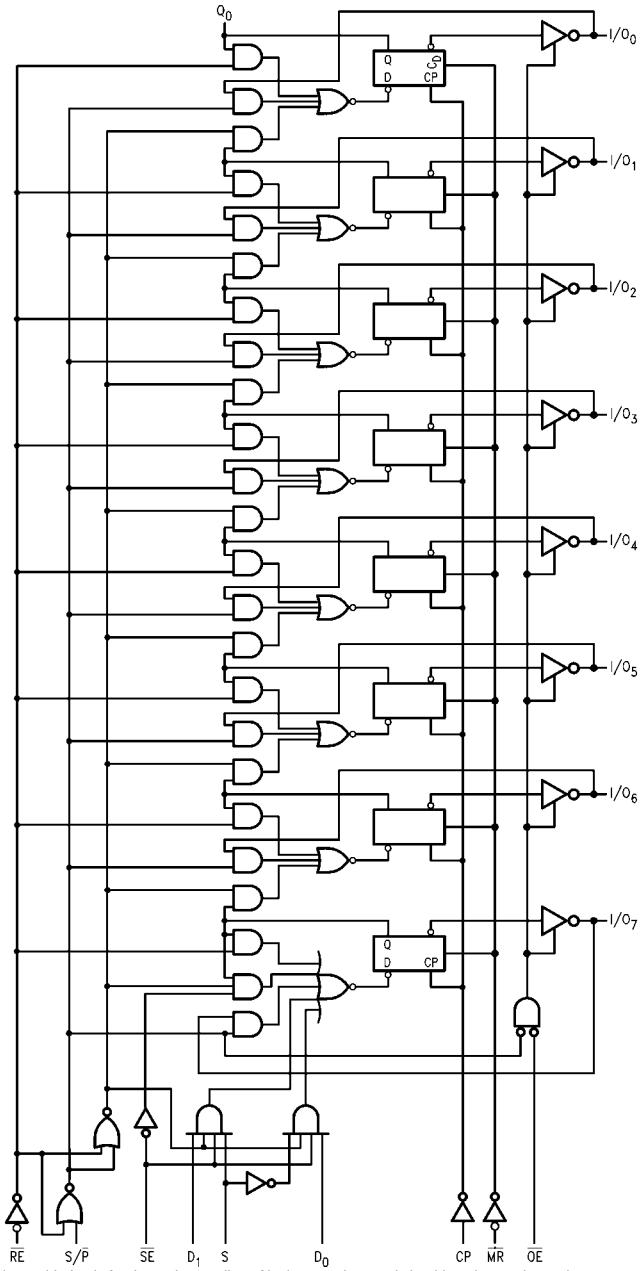
Note: I_7–I_0 = The level of the steady-state input at the respective I/O terminal is loaded into the flip-flop while the flip-flop outputs (except Q_0) are isolated from the I/O terminal.

Note: D_0, D_1 = The level of the steady-state inputs to the serial multiplexer input.

Note: O_7–O_0 = The level of the respective Q_n flip-flop prior to the last Clock LOW-to-HIGH transition.

Note 1: When the $\overline{OE}$ input is HIGH all I/O_n terminals are at the high impedance state; sequential operation or clearing of the register is not affected.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA (Q_0, I/O_n)
		10% V_{CC}	2.4					I_{OH} = −3 mA (I/O_n)
		5% V_{CC}	2.7					I_{OH} = −1 mA (Q_0, I/O_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (I/O_n)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA (Q_0)
		10% V_{CC}			0.5			I_{OL} = 24 mA (I/O_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (Non-I/O Inputs)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)				0.5	mA	Max	V_{IN} = 5.5V (I/O_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V ($\overline{RE}$, S/$\overline{P}$, D_n, CP, $\overline{MR}$, $\overline{OE}$)
					−1.2	mA	Max	V_{IN}= 0.5V (S)
					−1.8	mA	Max	V_{IN}= 0.5V ($\overline{SE}$)
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	$V_{I/O}$ = 2.7V (I/O_n)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	$V_{I/O}$ = 0.5V (I/O_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CC}	Power Supply Current			60	90	mA	Max	

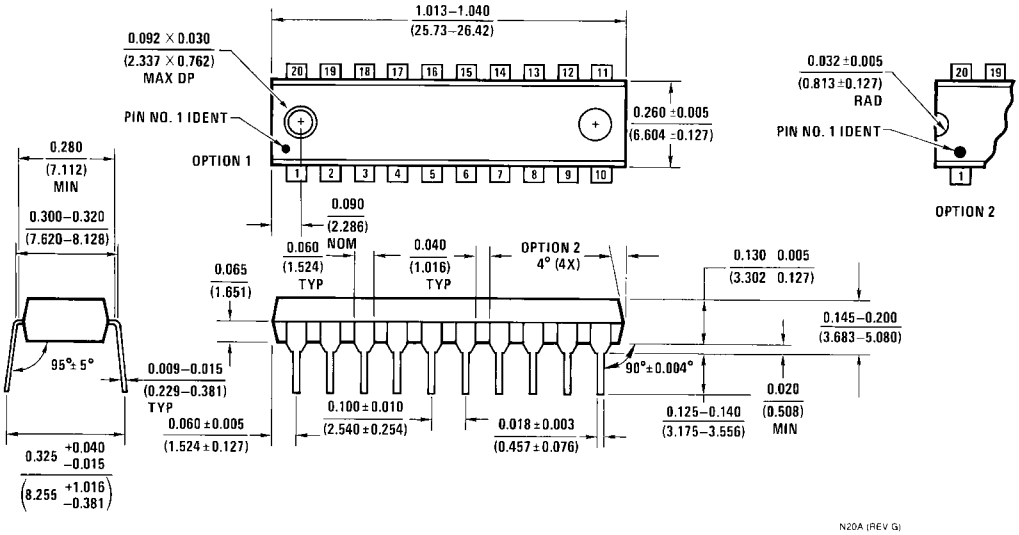
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		$T_A = 0°C$ to $+75°C$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	70	90		50		70		MHz
t_{PLH}	Propagation Delay	3.5	7.0	7.5	3.5	9.5	3.5	8.5	ns
t_{PHL}	CP to I/O_n	5.0	8.5	11.0	3.5	10.0	5.0	12.0	
t_{PLH}	Propagation Delay	3.5	7.0	9.0	3.5	11.0	3.5	10.0	
t_{PHL}	CP to Q_0	3.5	7.0	8.0	3.5	10.0	3.5	9.0	
t_{PHL}	Propagation Delay $\overline{MR}$ to I/O_n	6.0	10.0	13.0	6.0	15.0	6.0	14.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to Q_0	5.5	7.5	12.0	5.5	14.0	5.5	13.0	ns
t_{PZH}	Output Enable Time	3.0	6.5	9.0	3.0	12.5	3.0	10.0	ns
t_{PZL}	$\overline{OE}$ to I/O_n	4.0	8.5	11.0	4.0	14.5	4.0	12.0	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	2.0	8.0	2.0	7.0	
t_{PLZ}	$\overline{OE}$ to I/O_n	2.0	5.0	7.0	2.0	10.0	2.0	8.0	
t_{PZH}	Output Enable Time	4.5	8.0	10.5	4.5	13.5	4.5	11.5	ns
t_{PZL}	$S/\overline{P}$ to I/O_n	5.5	10.0	14.0	5.5	17.0	5.5	15.0	
t_{PHZ}	Output Disable Time	5.0	9.0	11.5	5.0	16.5	5.0	12.5	
t_{PLZ}	$S/\overline{P}$ to I/O_n	6.0	12.0	15.5	6.0	19.5	6.0	16.5	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$		$T_A = 0C$ to $+75°C$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	6.0		14.0		7.0		ns
$t_S(L)$	$\overline{RE}$ to CP	14.0		18.0		16.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		ns
$t_H(L)$	$\overline{RE}$ to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	6.5		8.5		7.5		ns
$t_S(L)$	D_0, D_1 or I/O_n to CP	6.5		8.5		7.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		3.0		3.0		ns
$t_H(L)$	D_0, D_1 or I/O_n to CP	2.0		3.0		3.0		
$t_SH)$	Setup Time, HIGH or LOW	7.0		9.0		8.0		ns
$t_S(L)$	$\overline{SE}$ to CP	2.5		11.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_H(L)$	$\overline{SE}$ to CP	0.0		1.0		0.0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		13.0		12.0		ns
$t_S(L)$	$S/\overline{P}$ to CP	13.5		21.0		15.5		
$t_S(H)$	Setup Time, HIGH or LOW	6.5		8.5		7.5		ns
$t_S(L)$	S to CP	9.0		11.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		1.0		0		ns
$t_H(L)$	S or $S/\overline{P}$ to CP	0		0		0		
$t_W(H)$	CP Pulse Width, HIGH or LOW	7.0		8.0		7.0		ns
$t_W(L)$								
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	5.5		7.5		6.5		
t_{REC}	Recovery Time $\overline{MR}$ to CP	8.0		12.0		8.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F323
Octal Universal Shift/Storage Register with Synchronous Reset and Common I/O Pins

General Description

The 74F323 is an 8-bit universal shift/storage register with 3-STATE outputs. Its function is similar to the 74F299 with the exception of Synchronous Reset. Parallel load inputs and flip-flop outputs are multiplexed to minimize pin count. Separate serial inputs and outputs are provided for Q_0 and Q_7 to allow easy cascading. Four operation modes are possible: hold (store), shift left, shift right and parallel load.

Features

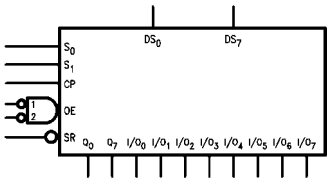
- Common parallel I/O for reduced pin count
- Additional serial inputs and outputs for expansion
- Four operating modes: shift left, shift right, load and store
- 3-STATE outputs for bus-oriented applications

Ordering Code:

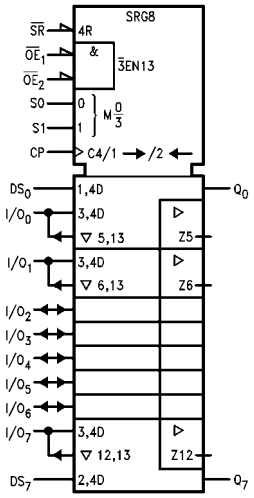
Order Number	Package Number	Package Description
74F323SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F323PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

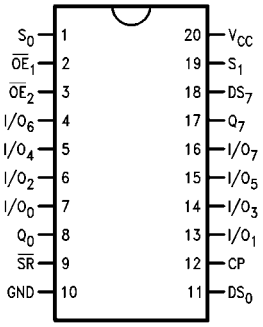
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
DS_0	Serial Data Input for Right Shift	1.0/1.0	20 µA/–0.6 mA
DS_7	Serial Data Input for Left Shift	1.0/1.0	20 µA/–0.6 mA
S_0, S_1	Mode Select Inputs	1.0/2.0	20 µA/–1.2 mA
$\overline{SR}$	Synchronous Reset Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs (Active LOW)	1.0/1.0	20 µA/–0.6 mA
I/O_0–I/O_7	Multiplexed Parallel Data Inputs	3.5/1.083	70 µA/–0.65 mA
	3-STATE Parallel Data Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)
Q_0, Q_7	Serial Outputs	50/33.3	–1 mA/20 mA

Functional Description

The 74F323 contains eight edge-triggered D-type flip-flops and the interstage logic necessary to perform synchronous reset, shift left, shift right, parallel load and hold operations. The type of operation is determined by S_0 and S_1 as shown in the Mode Select Table. All flip-flop outputs are brought out through 3-STATE buffers to separate I/O pins that also serve as data inputs in the parallel load mode. Q_0 and Q_7 are also brought out on other pins for expansion in serial shifting of longer words.

A LOW signal on $\overline{SR}$ overrides the Select inputs and allows the flip-flops to be reset by the next rising edge of CP. All other state changes are also initiated by the LOW-to-HIGH CP transition. Inputs can change when the clock is in either state provided only that the recommended setup and hold times, relative to the rising edge of CP, are observed.

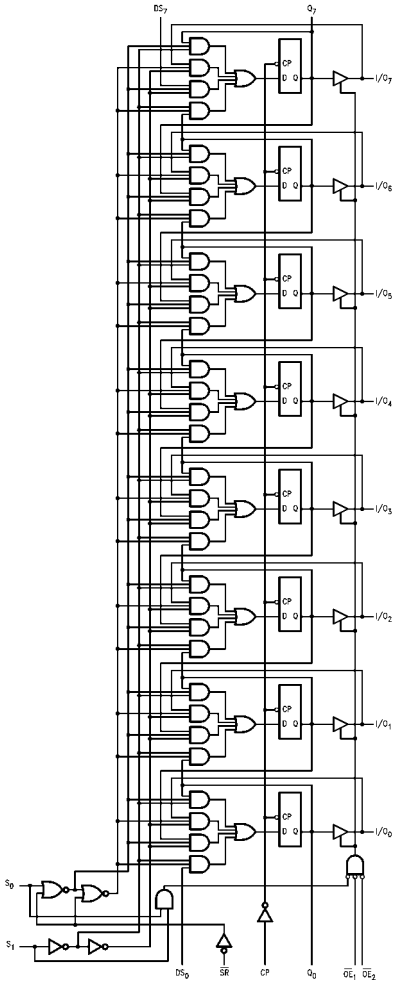
A HIGH signal on either $\overline{OE}_1$ or $\overline{OE}_2$ disables the 3-STATE buffers and puts the I/O pins in the high impedance state. In this condition the shift, load, hold and reset operations can still occur. The 3-STATE buffers are also disabled by HIGH signals on both S_0 and S_1 in preparation for a parallel load operation.

Mode Select Table

Inputs				Response
$\overline{SR}$	S_1	S_0	CP	
L	X	X	↗	Synchronous Reset; Q_0–Q_7 = LOW
H	H	H	↗	Parallel Load; $I/O_n \rightarrow Q_n$
H	L	H	↗	Shift Right; $DS_0 \rightarrow Q_0$, $Q_0 \rightarrow Q_1$, etc.
H	H	L	↗	Shift Left; $DS_7 \rightarrow Q_7$, $Q_7 \rightarrow Q_6$, etc.
H	L	L	X	Hold

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↗ = LOW-to-HIGH transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA (Q_0, Q_7)
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA (I/O_n)
		5% V_{CC}	2.7					I_{OH} = −1 mA (Q_0, Q_7)
		5% V_{CC}	2.7					I_{OH} = −3 mA (I/O_n)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA (Q_0, Q_7)
	Voltage	10% V_{CC}			0.5			I_{OL} = 24 mA (I/O_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (Non I/O Inputs)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (I/O Inputs)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (CP, DS_0, DS_7, $\overline{SR}$, $\overline{OE}_1$, $\overline{OE}_2$)
					−1.2	mA	Max	V_{IN} = 0.5V (S_0, S_1)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			68	95	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			68	95	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			68	95	mA	Max	V_O = HIGH Z

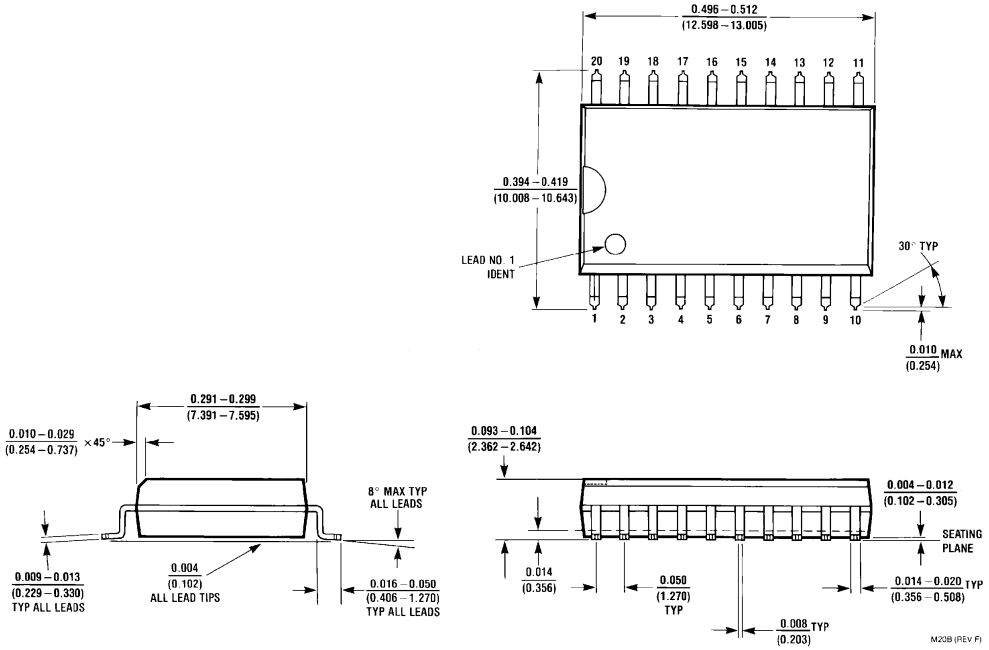
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Input Frequency	70	100		70		MHz
t_{PLH}	Propagation Delay	4.0	7.0	8.0	4.0	8.5	ns
t_{PHL}	CP to Q_0 or Q_7	4.5	6.5	8.0	4.5	8.5	
t_{PLH}	Propagation Delay	3.5	7.0	9.0	3.5	10.0	ns
t_{PHL}	CP to I/O_n	4.0	8.5	9.0	4.0	10.0	
t_{PZH}	Output Enable Time	3.5	6.0	8.0	3.5	9.0	ns
t_{PZL}		4.0	7.0	10.0	4.0	11.0	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	2.0	7.0	ns
t_{PLZ}		1.0	4.0	5.5	1.0	6.5	
t_{PZH}	Output Enable Time	3.5		9.0	3.5	10.0	ns
t_{PZL}	S_n to I/O_n	4.0		10.0	4.0	11.0	
t_{PHZ}	Output Disable Time	2.5		6.0	2.5	7.0	ns
t_{PLZ}	S_n to I/O_n	1.0		5.5	1.5	6.5	

AC Operating Requirements

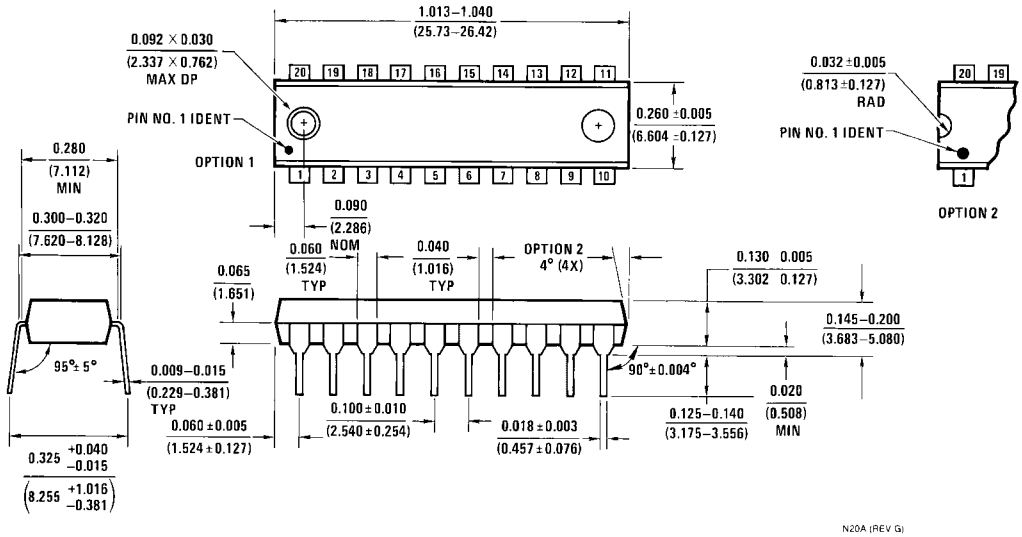
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	8.5		8.5		ns
$t_S(L)$	S_0 or S_1 to CP	8.5		8.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	S_0 or S_1 to CP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	5.0		5.0		ns
$t_S(L)$	I/O_n, DS_0, DS_7 to CP	5.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		
$t_H(L)$	I/O_n, DS_0, DS_7 to CP	2.0		2.0		
$t_S(H)$	Setup Time, HIGH or LOW	10.0		10.0		ns
$t_S(L)$	$\overline{SR}$ to CP	10.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	$\overline{SR}$ to CP	0		0		
$t_W(H)$	CP Pulse Width	5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F350
4-Bit Shifter with 3-STATE Outputs

General Description

The 74F350 is a specialized multiplexer that accepts a 4-bit word and shifts it 0, 1, 2 or 3 places, as determined by two Select (S_0, S_1) inputs. For expansion to longer words, three linking inputs are provided for lower-order bits; thus two packages can shift an 8-bit word, four packages a 16-bit word, etc. Shifting by more than three places is accomplished by paralleling the 3-STATE outputs of different packages and using the Output Enable ($\overline{OE}$) inputs as a third Select level. With appropriate interconnections, the 74F350 can perform zero-backfill, sign-extend or end-around (barrel) shift functions.

Features

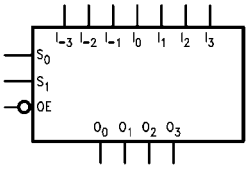
- Linking inputs for word expansion
- 3-STATE outputs for extending shift range

Ordering Code:

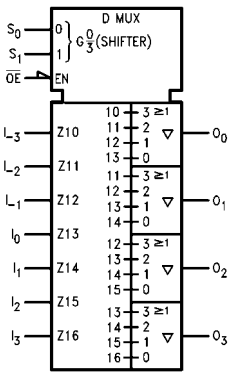
Order Number	Package Number	Package Description
74F350SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F350SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F350PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

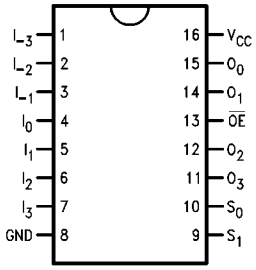
Logic Symbols



IEEE/IEC



Connection Diagram



Truth Table

Inputs			Outputs			
$\overline{OE}$	S_1	S_0	O_0	O_1	O_2	O_3
H	X	X	Z	Z	Z	Z
L	L	L	I_0	I_1	I_2	I_3
L	L	H	I_{-1}	I_0	I_1	I_2
L	H	L	I_{-2}	I_{-1}	I_0	I_1
L	H	H	I_{-3}	I_{-2}	I_{-1}	I_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0, S_1	Select Inputs	1.0/2.0	20 µA/–1.2 mA
I_{-3}–I_3	Data Inputs	1.0/2.0	20 µA/–1.2 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
O_0–O_3	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

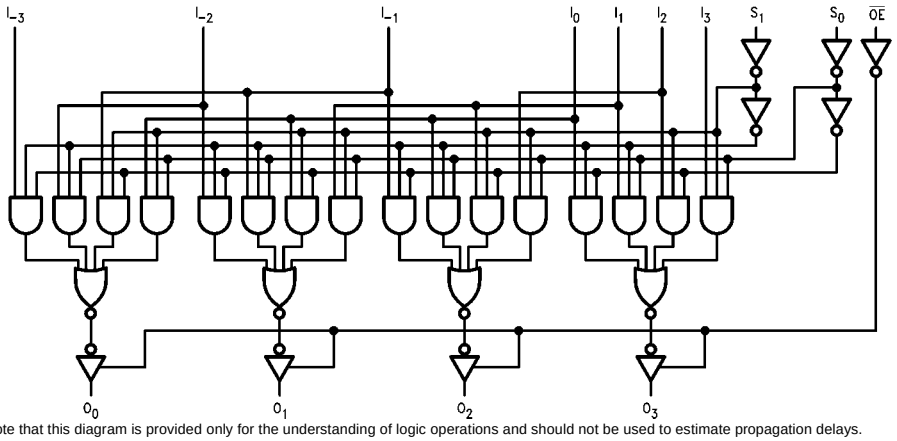
The 74F350 is operationally equivalent to a 4-input multiplexer with the inputs connected so that the select code causes successive one-bit shifts of the data word. This internal connection makes it possible to perform shifts of 0, 1, 2 or 3 places on words of any length.

A 4-bit data word is introduced at the I_n inputs and is shifted according to the code applied to the select inputs S_0, S_1. Outputs O_0–O_3 are 3-STATE, controlled by an active LOW output enable ($\overline{OE}$). When $\overline{OE}$ is LOW, data outputs will follow selected data inputs; when HIGH, the data outputs will be forced to the high impedance state. This feature allows shifters to be cascaded on the same output lines or to a common bus. The shift function can be logical, with zeros pulled in at either or both ends of the shifting field; arithmetic, where the sign bit is repeated during a shift down; or end around, where the data word forms a continuous loop.

Logic Equations

$$O_0 = \overline{S}_0\overline{S}_1I_0 + S_0\overline{S}_1I_{-1} + \overline{S}_0S_1I_{-2} + S_0S_1I_{-3}$$
$$O_1 = \overline{S}_0\overline{S}_1I_1 + S_0\overline{S}_1I_0 + \overline{S}_0S_1I_{-1} + S_0S_1I_{-2}$$
$$O_2 = \overline{S}_0\overline{S}_1I_2 + S_0\overline{S}_1I_1 + \overline{S}_0S_1I_0 + S_0S_1I_{-1}$$
$$O_3 = \overline{S}_0\overline{S}_1I_3 + S_0\overline{S}_1I_2 + \overline{S}_0S_1I_1 + S_0S_1I_0$$

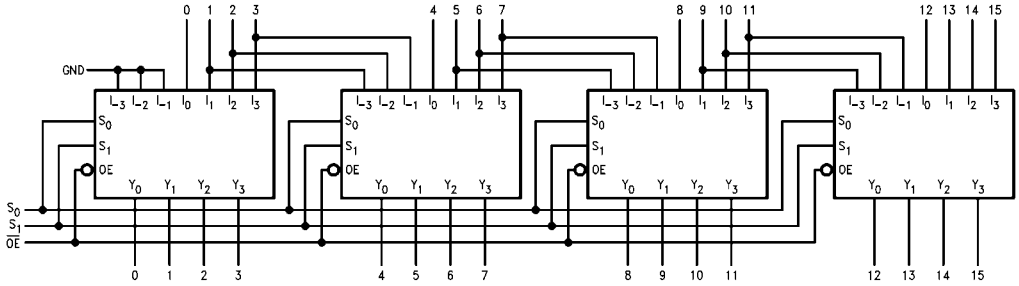
Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Applications

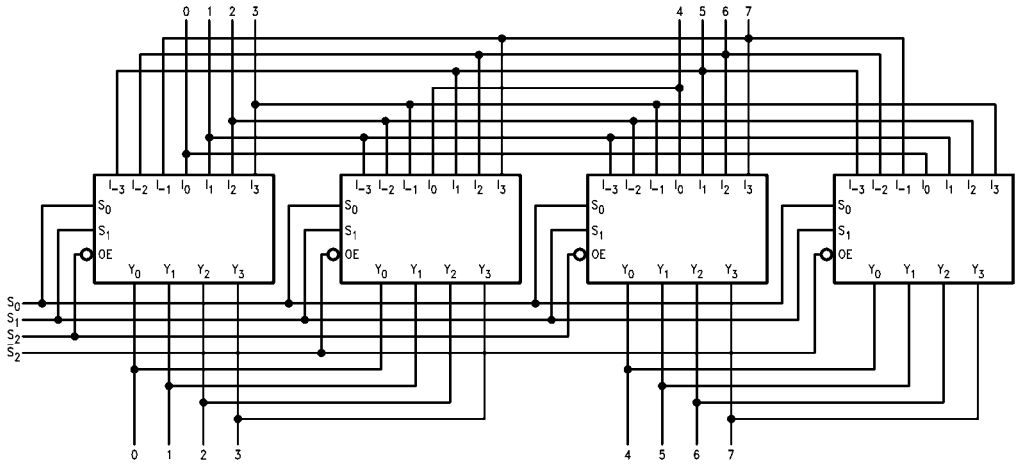
16-Bit Shift-Up 0 to 3 Places, Zero Backfill



Function Table

S_1	S_0	Shift Function
L	L	No Shift
L	H	Shift 1 Place
H	L	Shift 2 Places
H	H	Shift 3 Places

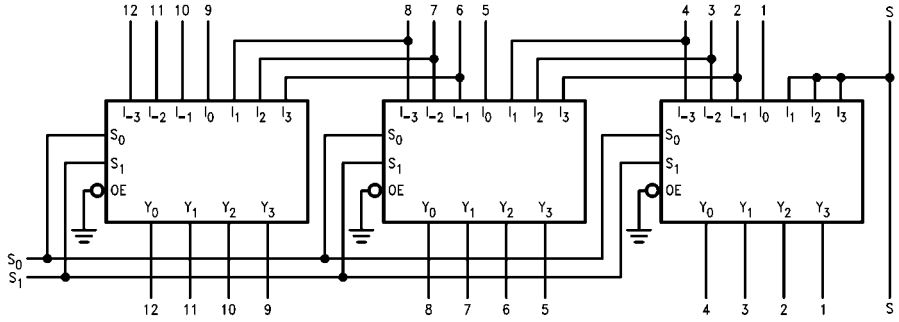
8-Bit End Around Shift 0 to 7 Places



Function Table

S_2	S_1	S_0	Shift Function
L	L	L	No Shift
L	L	H	Shift End Around 1
L	H	L	Shift End Around 2
L	H	H	Shift End Around 3
H	L	L	Shift End Around 4
H	L	H	Shift End Around 5
H	H	L	Shift End Around 6
H	H	H	Shift End Around 7

13-Bit Twos Complement Scaler



Function Table

S_1	S_0	Scale
L	L÷8	$^1/_8$
L	H÷4	$^1/_4$
H	L÷2	½
H	H No Change	1

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

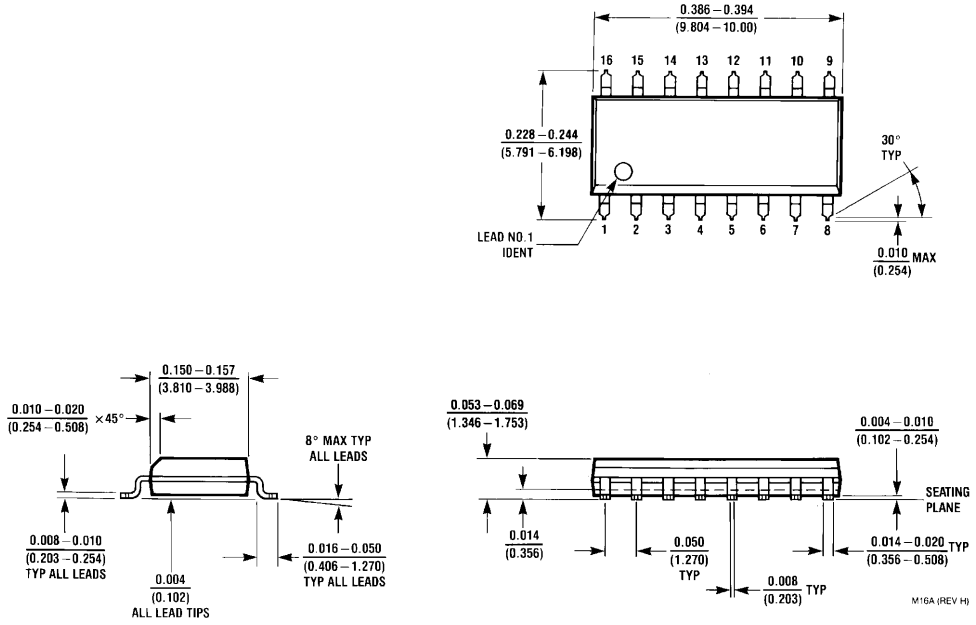
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		10% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.2	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			34	42	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			40	57	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			40	57	mA	Max	V_O = HIGH Z

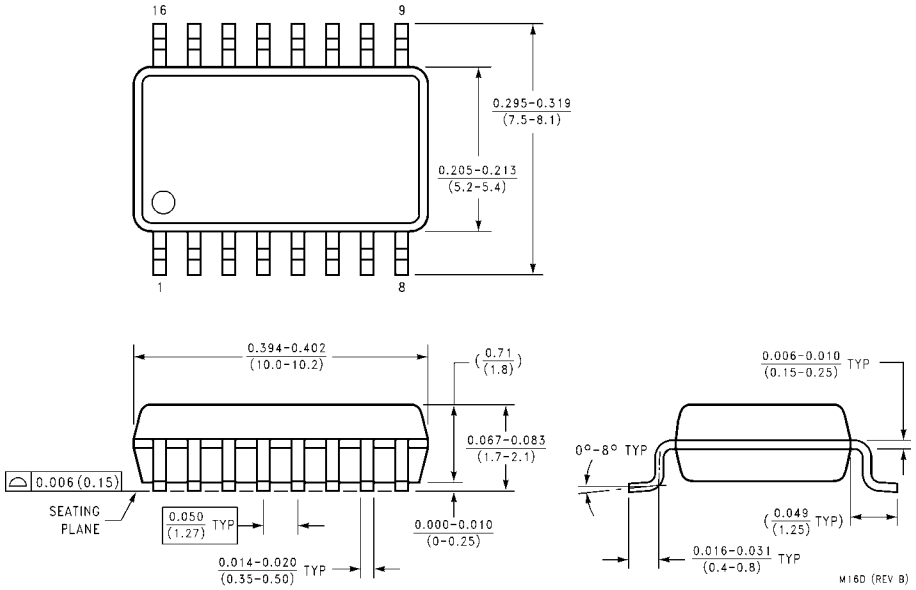
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	4.5	6.0	3.0	7.0	ns
t_{PHL}	I_n to O_n	2.5	4.0	5.5	2.5	6.5	
t_{PLH}	Propagation Delay	4.0	7.8	10.0	4.0	13.5	ns
t_{PHL}	S_n to O_n	3.0	6.5	8.5	3.0	9.5	
t_{PZH}	Output Enable Time	2.5	5.0	7.0	2.5	8.0	ns
t_{PZL}		4.0	7.0	9.0	4.0	10.0	
t_{PHZ}	Output Disable Time	2.0	3.9	5.5	2.0	6.5	
t_{PLZ}		2.0	4.0	5.5	2.0	7.5	

Physical Dimensions inches (millimeters) unless otherwise noted

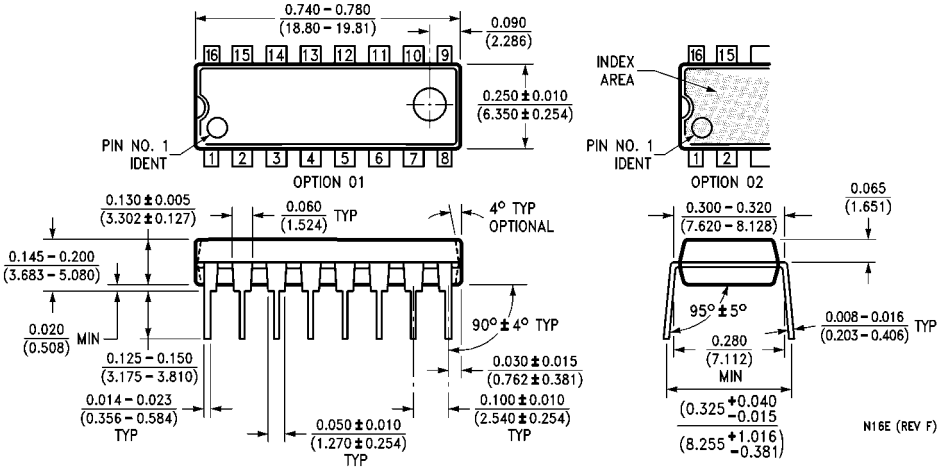


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

May 1988
Revised August 1999

74F352
Dual 4-Input Multiplexer

General Description

The 74F352 is a very high-speed dual 4-input multiplexer with common Select inputs and individual Enable inputs for each section. It can select two bits of data from four sources. The two buffered outputs present data in the inverted (complementary) form. The 74F352 is the functional equivalent of the 74F153 except with inverted outputs.

Features

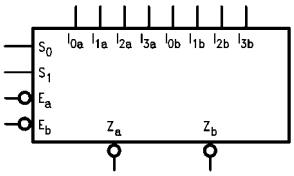
- Inverted version of 74F153
- Separate enables for each multiplexer
- Input clamp diode limits high speed termination effects

Ordering Code:

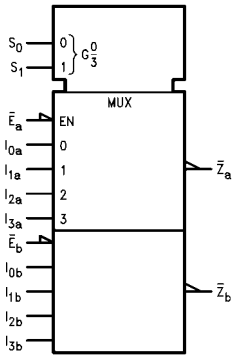
Order Number	Package Number	Package Description
74F352SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F352PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

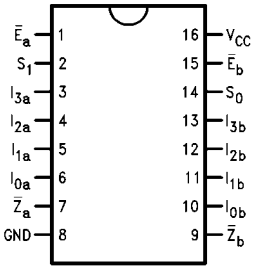
Logic Symbols



IEEE/IEC



Connection Diagram



Truth Table

Select Inputs		Inputs (a or b)					Output
S_0	S_1	$\bar{E}$	I_0	I_1	I_2	I_3	$\bar{Z}$
X	X	H	X	X	X	X	H
L	L	L	L	X	X	X	H
L	L	L	H	X	X	X	L
H	L	L	X	L	X	X	H
H	L	L	X	H	X	X	L
L	H	L	X	X	L	X	H
L	H	L	X	X	H	X	L
H	H	L	X	X	X	L	H
H	H	L	X	X	X	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I_{0a}–I_{3a}	Side A Data Inputs	1.0/1.0	20 μA/–0.6 mA
I_{0b}–I_{3b}	Side B Data Inputs	1.0/1.0	20 μA/–0.6 mA
S_0–S_1	Common Select Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{E}_a$	Side A Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{E}_b$	Side B Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{Z}_a$, $\overline{Z}_b$	Multiplexer Outputs (Inverted)	50/33.3	–1 mA/20 mA

Functional Description

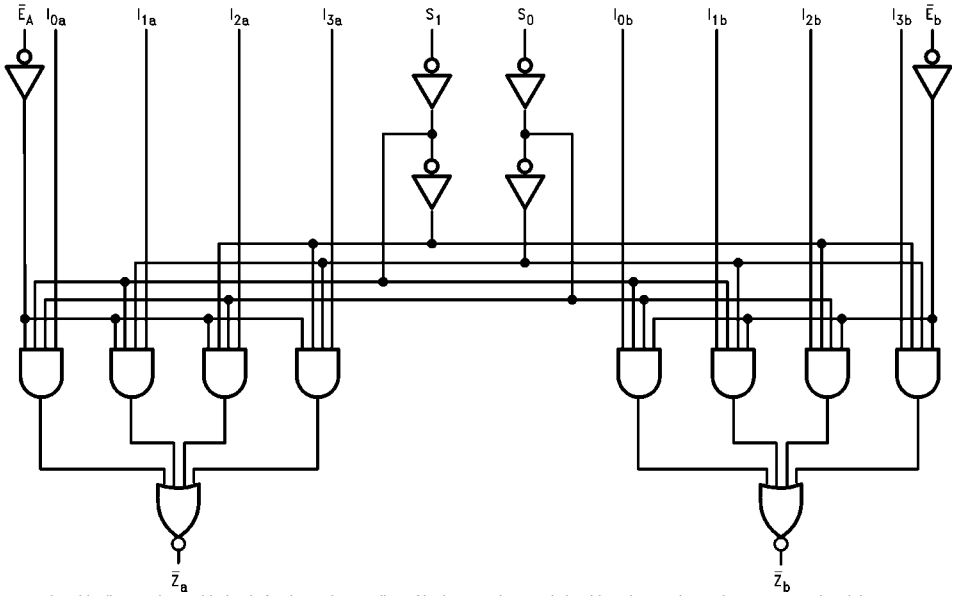
The 74F352 is a dual 4-input multiplexer. It selects two bits of data from up to four sources under the control of the common Select inputs (S_0, S_1). The two 4-input multiplexer circuits have individual active LOW Enables ($\overline{E}_a$, $\overline{E}_b$) which can be used to strobe the outputs independently. When the Enables ($\overline{E}_a$, $\overline{E}_b$) are HIGH, the corresponding outputs ($\overline{Z}_a$, $\overline{Z}_b$) are forced HIGH. The logic equations for the outputs are shown below:

$$\overline{Z}_a = \overline{E}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet S_0 + I_{3a} \bullet S_1 \bullet S_0)$$

$$\overline{Z}_b = \overline{E}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet S_0 + I_{3b} \bullet S_1 \bullet S_0)$$

The 74F352 can be used to move data from a group of registers to a common output bus. The particular register from which the data came would be determined by the state of the Select inputs. A less obvious application is as a function generator. The 74F352 can generate two functions of three variables. This is useful for implementing highly irregular random logic.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

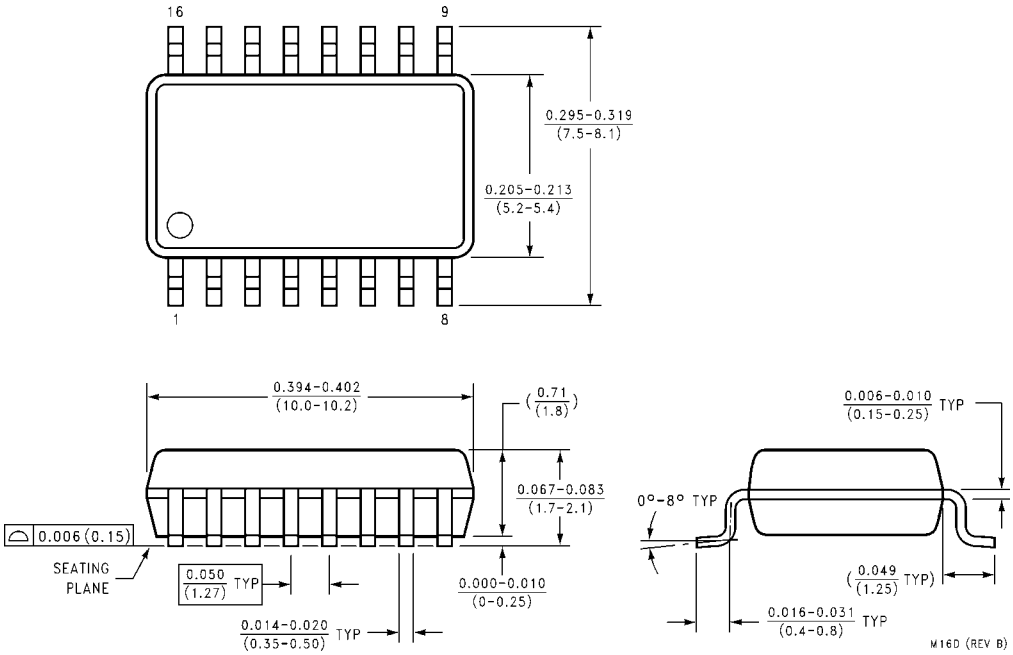
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			9.3	14	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			13.3	20	mA	Max	V_O = LOW

AC Electrical Characteristics

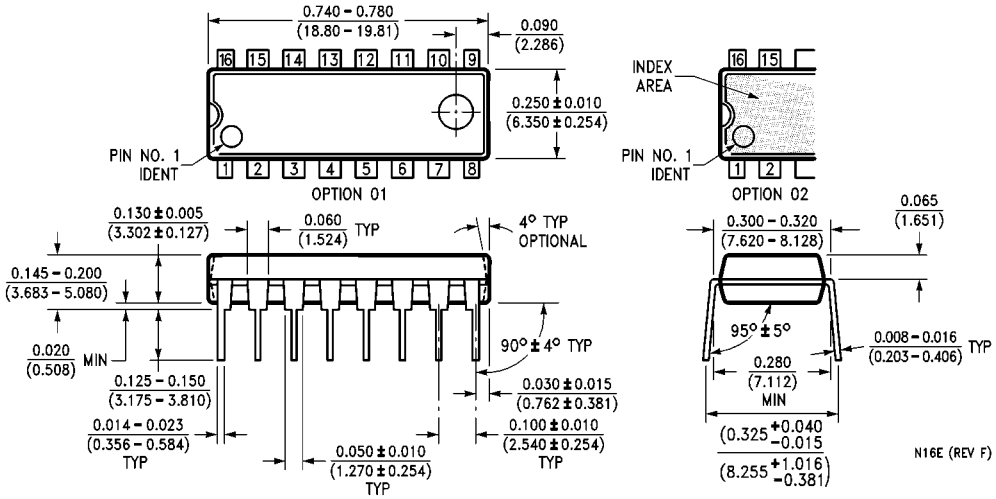
Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0	8.0	11.0	3.5	12.5	ns
t_{PHL}	S_n to $\overline{Z}_n$	3.5	6.5	8.5	3.0	9.5	
t_{PLH}	Propagation Delay	3.0	4.5	6.0	2.5	7.0	ns
t_{PHL}	$\overline{E}_n$ to $\overline{Z}_n$	3.0	5.0	7.0	2.5	8.0	
t_{PLH}	Propagation Delay	2.0	5.2	7.0	2.0	8.0	ns
t_{PHL}	I_n to $\overline{Z}_n$	1.3	2.5	4.0	1.0	4.5	

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F365
Hex Buffer/Driver with 3-STATE Outputs

General Description

The 74F365 is a hex buffer and line driver designed to be employed as a memory and address driver, clock driver and bus-oriented transmitter/receiver.

Features

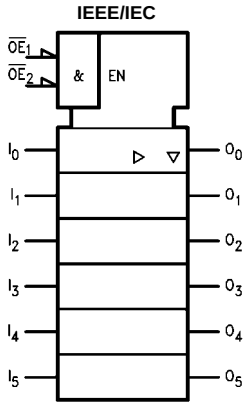
- 3-STATE buffer outputs
- Outputs sink 64 mA
- Bus-oriented

Ordering Code:

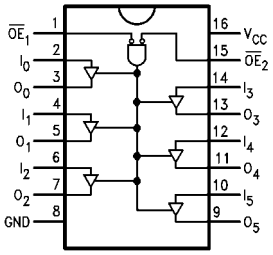
Order Number	Package Number	Package Description
74F365SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F365PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Function Table

Inputs			Output
$\overline{OE}_1$	$\overline{OE}_2$	I	O
L	L	L	L
L	L	H	H
X	H	X	Z
H	X	X	Z

L = LOW Voltage Level
H = HIGH Voltage Level
X = Immaterial
Z = High Impedance

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)	1.0/0.033	20 μA/20 μA
I_n	Inputs	1.0/0.033	20 μA/20 μA
O_n	Outputs	600/106.6 (80)	−12 mA/64 mA (48 mA)

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

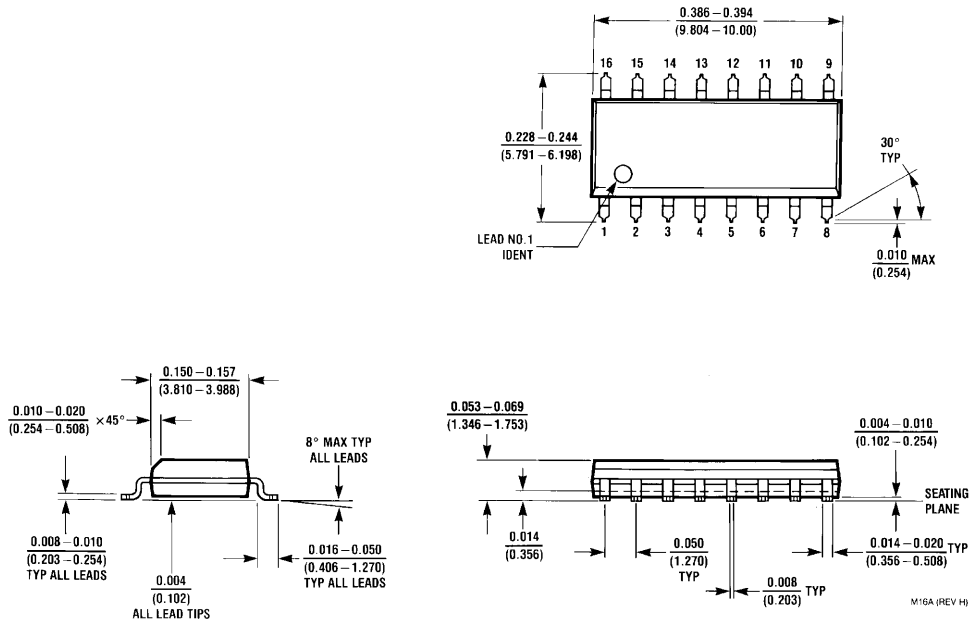
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.4					I_{OH} = −3 mA
	Voltage	10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				20	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	0.0	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−20	µA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			25	35	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			44	62	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			35	48	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

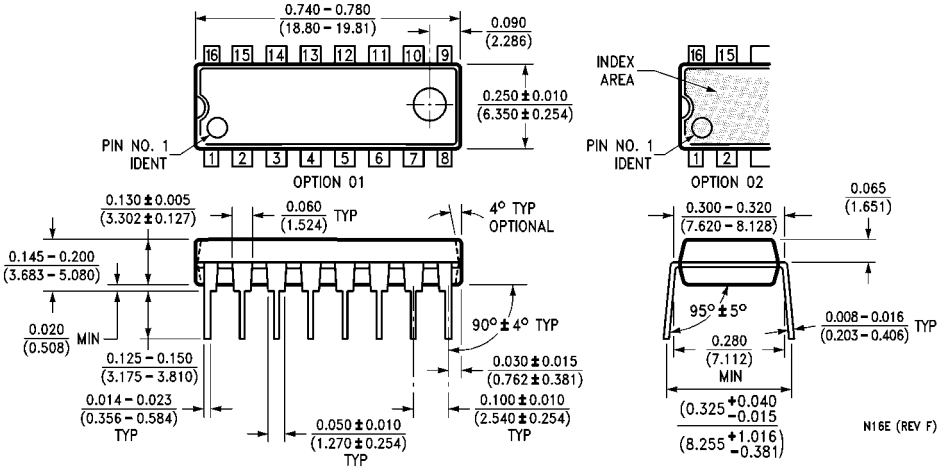
Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = −55°C to +125°C, V_{CC} = +5.0V, C_L = 50 pF		T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.6	6.5	2.0	7.0	2.0	7.0	ns
t_{PHL}	I_n to O_n	2.5	4.9	7.0	2.0	7.0	2.0	7.5	
t_{PZH}	Enable Time	2.5	5.1	9.5	2.0	8.5	2.5	10.0	ns
t_{PZL}		2.5	5.7	9.0	2.0	8.5	2.5	9.5	
t_{PHZ}	Disable Time	2.0	3.6	6.5	1.5	6.5	2.0	7.0	ns
t_{PLZ}		2.0	4.4	6.5	1.5	9.0	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead (0.150' Wide) Molded Small Outline Package, JEDEC (S)
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F366•74F368
Hex Inverter Buffer with 3-STATE Outputs

Features

- 3-STATE buffer outputs sink 64 mA
- High-speed
- Bus-oriented
- High impedance npn base inputs for reduced loading

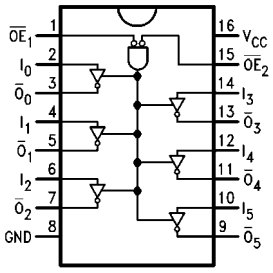
Ordering Code:

Order Number	Package Number	Package Description
74F366SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F366PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F368SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F368SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F368PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

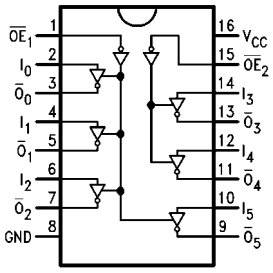
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

74F366

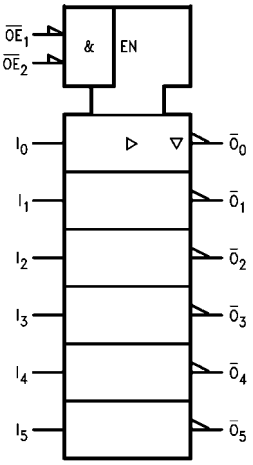


74F368

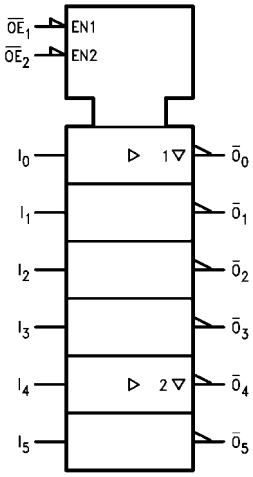


Logic Symbols

IEEE/IEC
74F366



IEEE/IEC
74F368



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)	1.0/0.033	20 μA/–20 μA
I_n	Input	1.0/0.033	20 μA/–20 μA
O_n, $\overline{O}_n$	Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Function Tables

74F366

Inputs			Output
$\overline{OE}_1$	$\overline{OE}_2$	I	$\overline{O}$
L	L	L	H
L	L	H	L
X	H	X	Z
H	X	X	Z

74F368

Inputs		Output
$\overline{OE}$	I	$\overline{O}$
L	L	H
L	H	L
H	X	Z

L = LOW Voltage Level X = Immaterial
H = HIGH Voltage Level Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

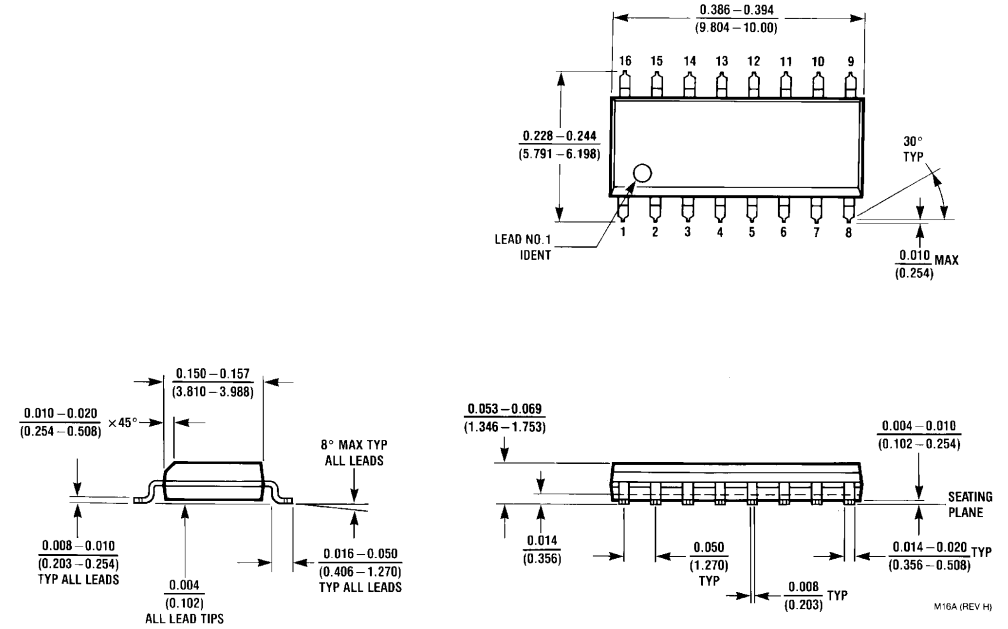
DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH 10% V_{CC} Voltage	2.0			V	Min	I_{OH} = −15 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			20	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			100	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−20	µA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current			50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current			250	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		20	25	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		49	62	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		35	48	mA	Max	V_O = HIGH Z

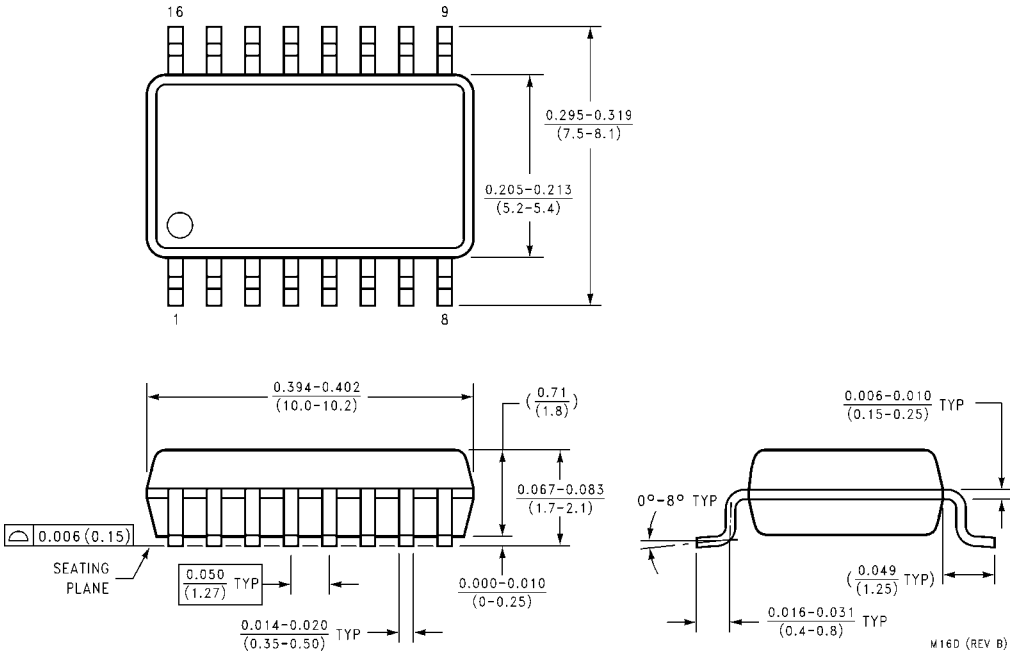
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.0	6.5	2.0	7.5	ns
t_{PHL}		1.0	1.8	5.0	1.0	5.5	
t_{PZH}	Enable Time (74F366)	2.5	4.2	9.5	2.5	10.0	ns
t_{PZL}		2.5	4.2	9.0	2.5	9.5	
t_{PZH}	Enable Time (74F368)	2.5	4.2	7.5	2.0	8.5	ns
t_{PZL}		3.0	5.6	8.5	3.0	9.0	
t_{PHZ}	Disable Time	2.0	3.3	6.5	2.0	7.0	ns
t_{PLZ}		2.0	4.1	6.5	2.0	7.0	

Physical Dimensions inches (millimeters) unless otherwise noted

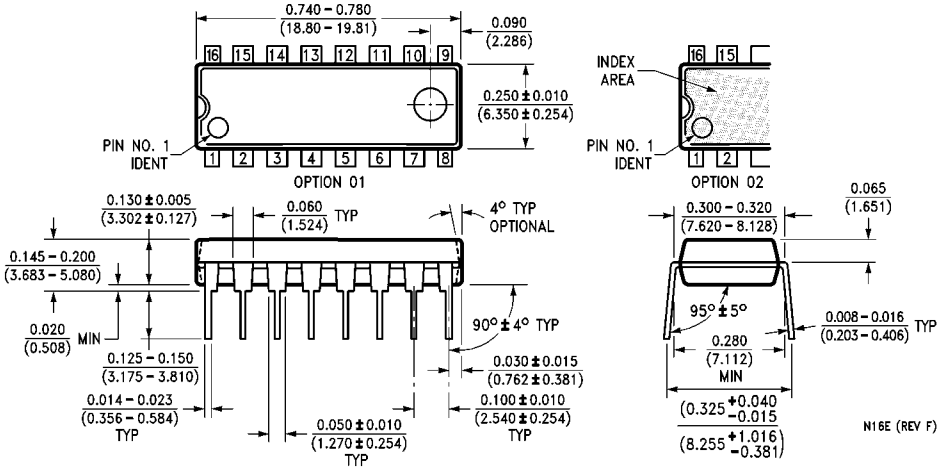


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised March 1999

74F37
Quad Two-Input NAND Buffer

General Description

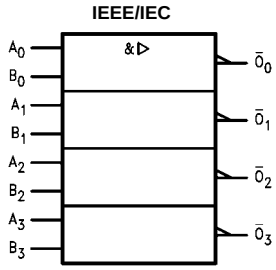
This device contains four independent gates, each of which performs the logic NAND function.

Ordering Code:

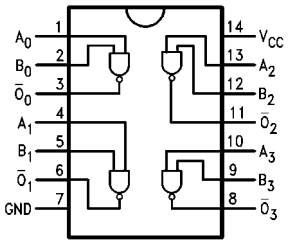
Order Number	Package Number	Package Description
74F37SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F37SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F37PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/2.0	20 µA/–1.2 mA
$\overline{O}_n$	Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Function Table

Inputs		Output
A	B	$\overline{O}$
L	L	H
L	H	H
H	L	H
H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

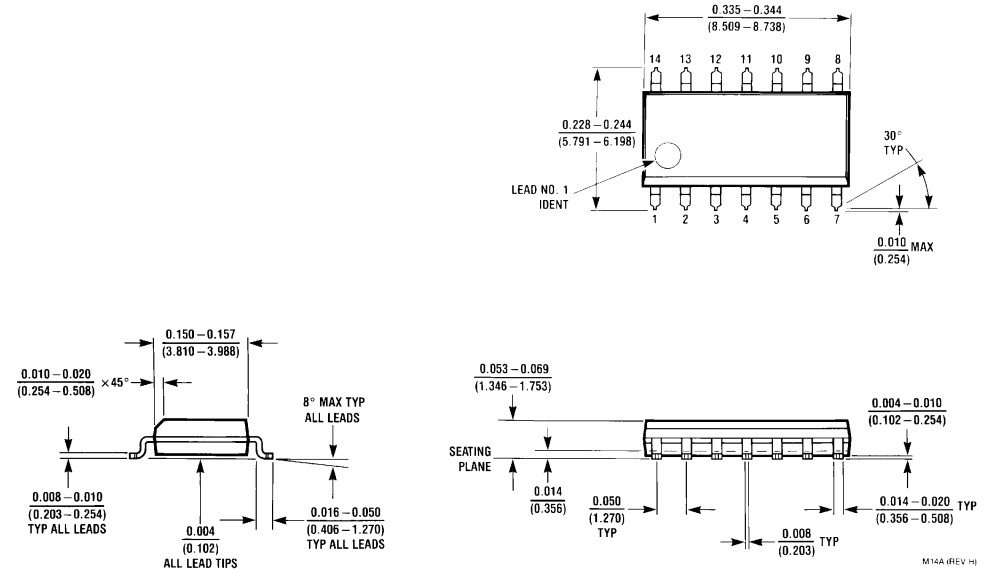
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.4					I_{OH} = −3 mA
	Voltage	10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.2	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			3.7	6.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			28.0	33.0	mA	Max	V_O = LOW

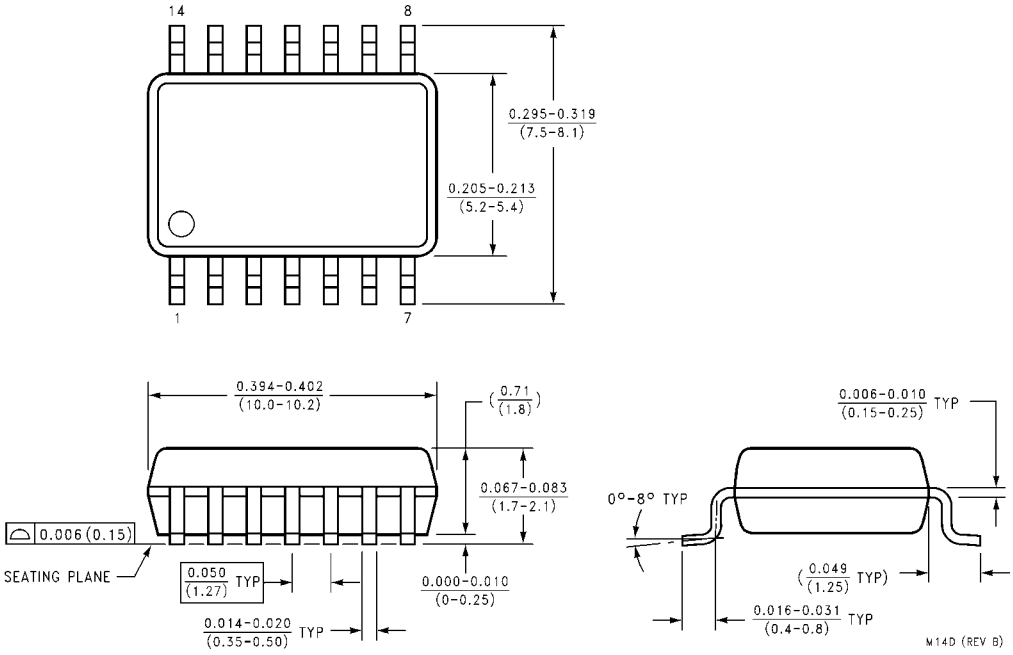
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.0	3.2	5.5	1.5	6.5	ns
t_{PHL}	A_n, B_n to $\overline{O}_n$	1.5	2.4	4.5	1.0	5.0	

Physical Dimensions inches (millimeters) unless otherwise noted

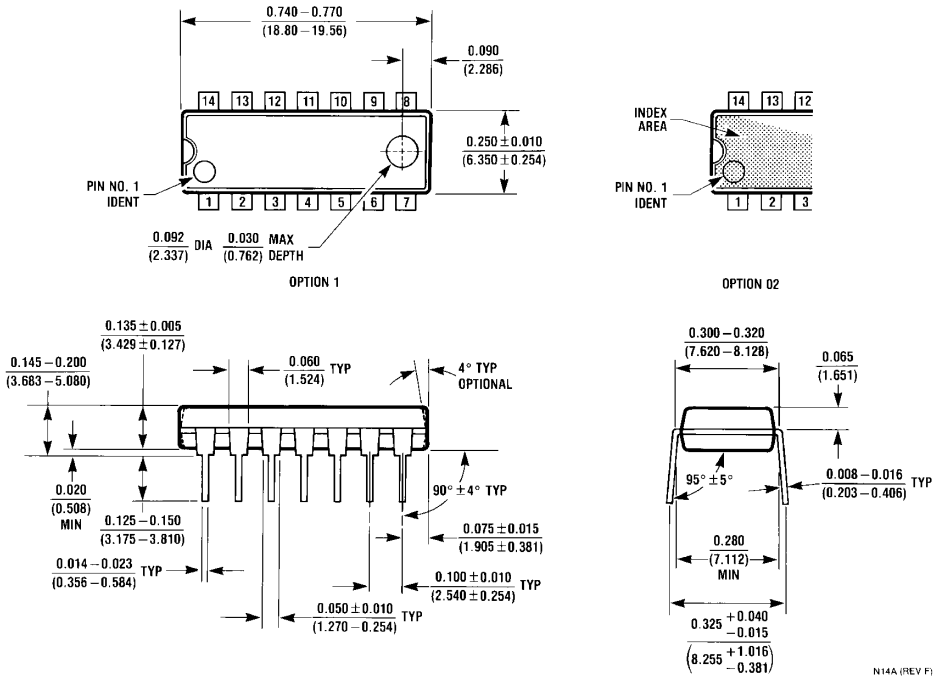


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1988
Revised August 1999

74F373
Octal Transparent Latch with 3-STATE Outputs

General Description

The 74F373 consists of eight latches with 3-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

Features

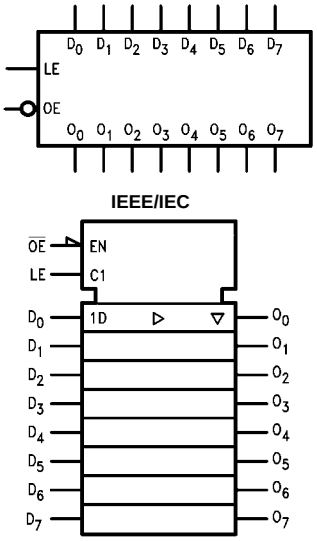
- Eight latches in a single package
- 3-STATE outputs for bus interfacing
- Guaranteed 4000V minimum ESD protection

Ordering Code:

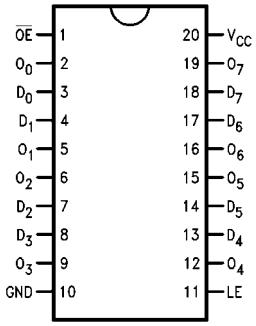
Order Number	Package Number	Package Description
74F373SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F373MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F373PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 µA/–0.6 mA
LE	Latch Enable Input (Active HIGH)	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
O_0–O_7	3-STATE Latch Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

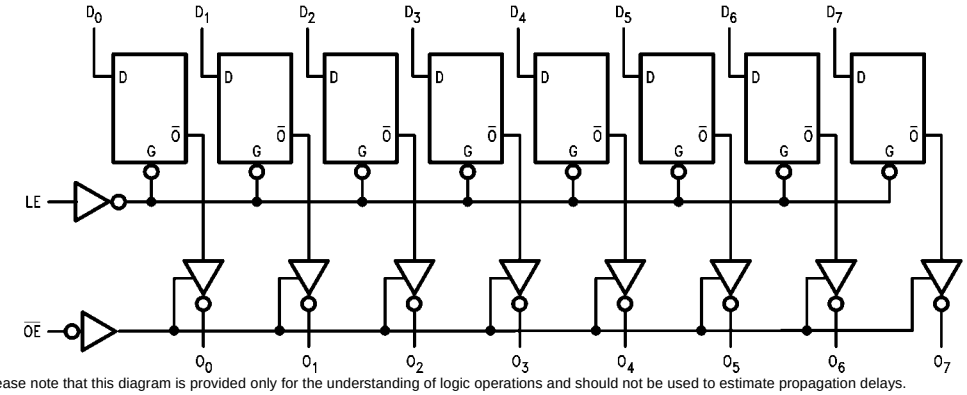
The 74F373 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Output
LE	$\overline{OE}$	D_n	O_n
H	L	H	H
H	L	L	L
L	L	X	O_n (no change)
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance State

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			38	55	mA	Max	V_O = HIGH Z

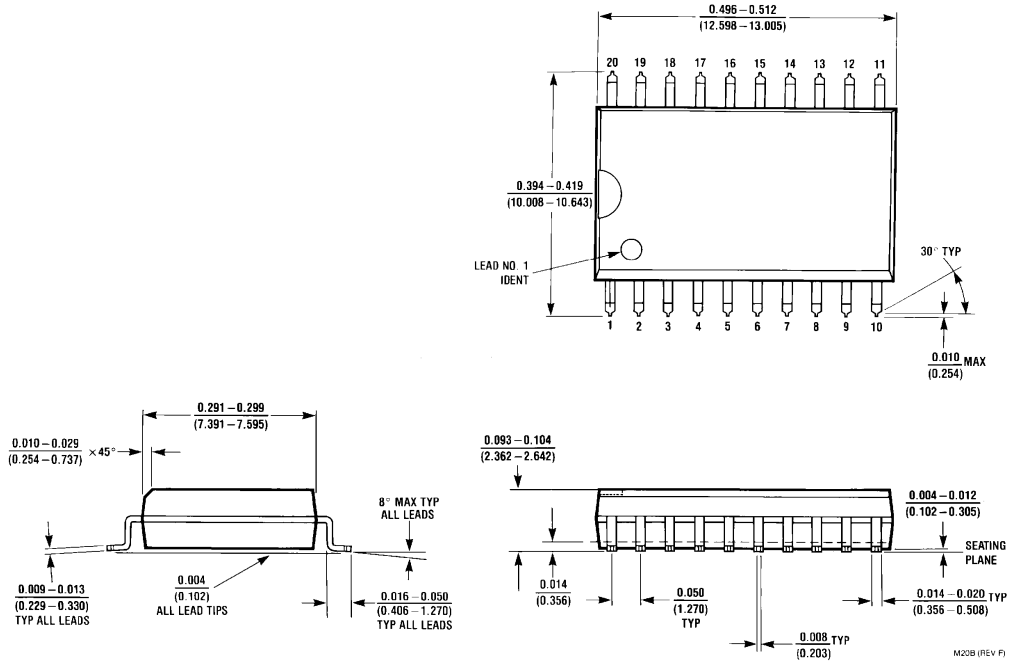
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	5.3	7.0	3.0	8.5	3.0	8.0	ns
t_{PHL}	D_n to O_n	2.0	3.7	5.0	2.0	7.0	2.0	6.0	
t_{PLH}	Propagation Delay	5.0	9.0	11.5	5.0	15.0	5.0	13.0	ns
t_{PHL}	LE to O_n	3.0	5.2	7.0	3.0	8.5	3.0	8.0	
t_{PZH}	Output Enable Time	2.0	5.0	11.0	2.0	13.5	2.0	12.0	ns
t_{PZL}		2.0	5.6	7.5	2.0	10.0	2.0	8.5	
t_{PHZ}	Output Disable Time	1.5	4.5	6.5	1.5	10.0	1.5	7.5	ns
t_{PLZ}		1.5	3.8	5.0	1.5	7.0	1.5	6.0	

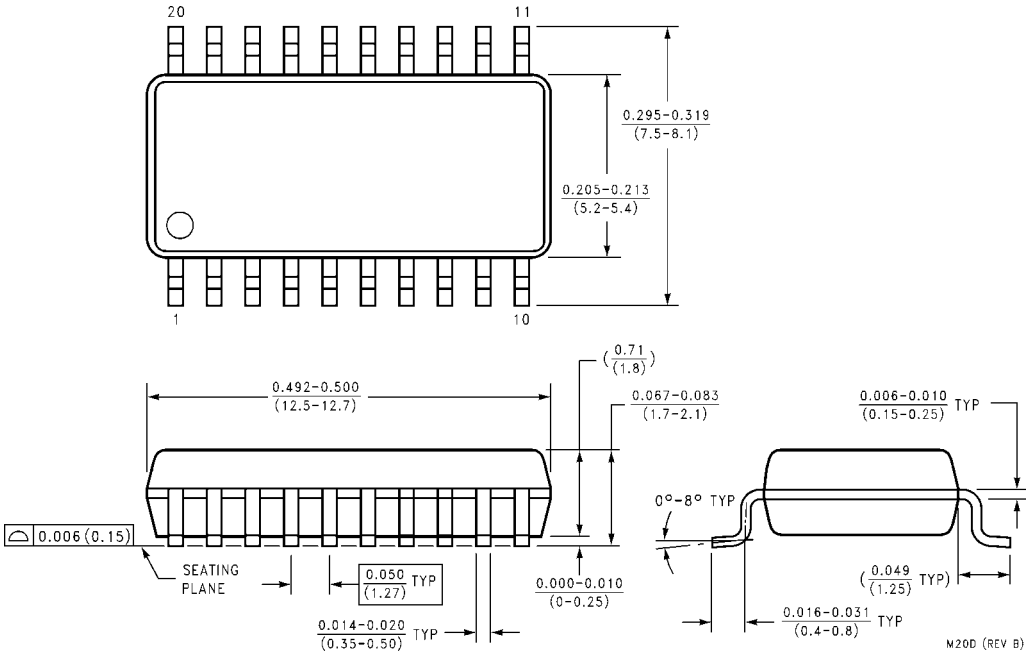
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_S(L)$	D_n to LE	2.0		2.0		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.0		3.0		
$t_H(L)$	D_n to LE	3.0		4.0		3.0		
$t_W(H)$	LE Pulse Width, HIGH	6.0		6.0		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

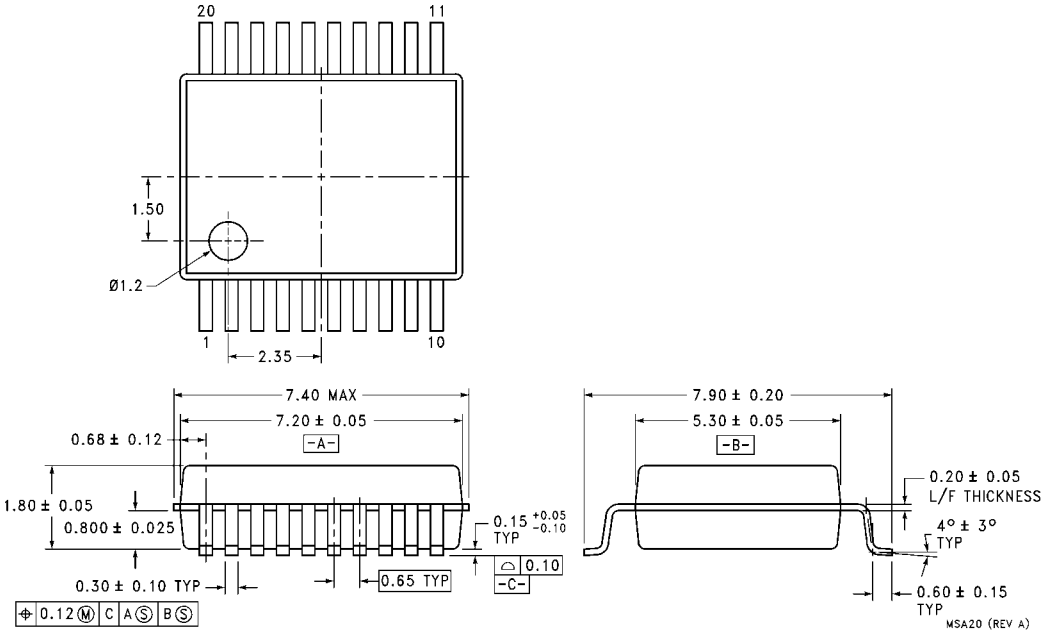


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



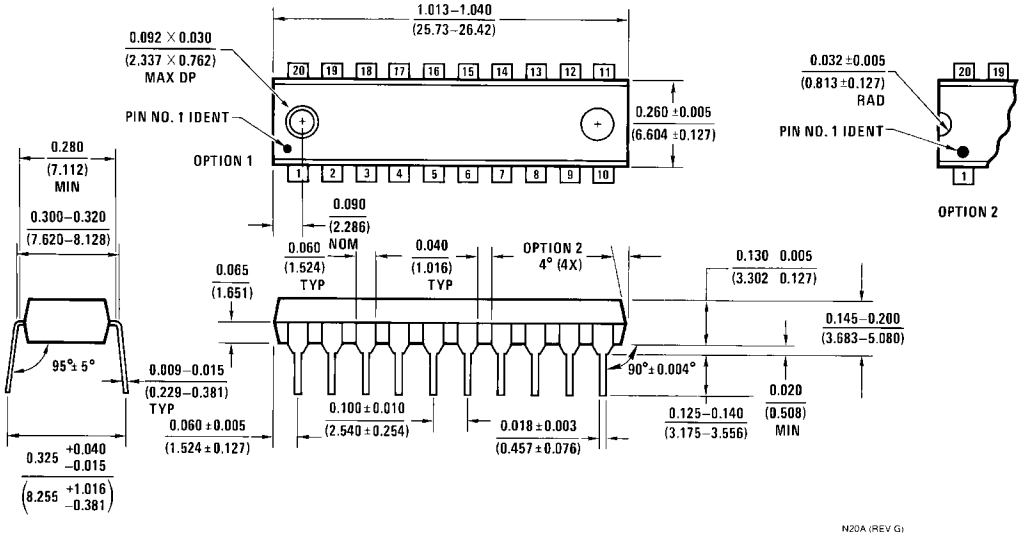
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

May 1988
Revised August 1999

74F374
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The 74F374 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

Features

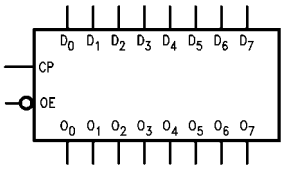
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- 3-STATE outputs for bus-oriented applications
- Guaranteed 4000V minimum ESD protection

Ordering Code:

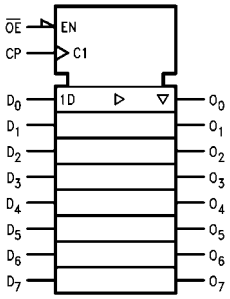
Order Number	Package Number	Package Description
74F374SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F374MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F374PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

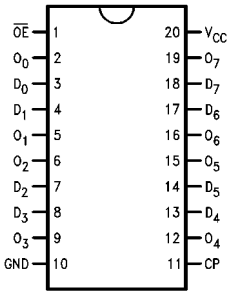
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
O_0–O_7	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

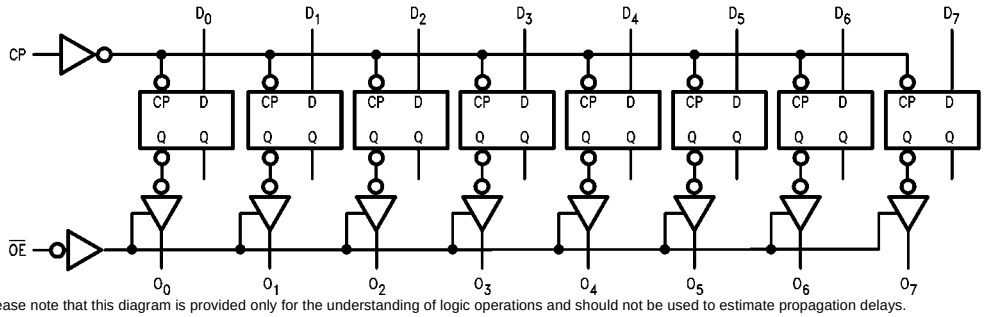
The 74F374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affected the state of the flip-flops.

Truth Table

Inputs			Internal	Output
D_n	CP	$\overline{OE}$	Register	O_n
H	⌐	L	H	H
L	⌐	L	L	L
X	X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			55	86	mA	Max	V_O = HIGH Z

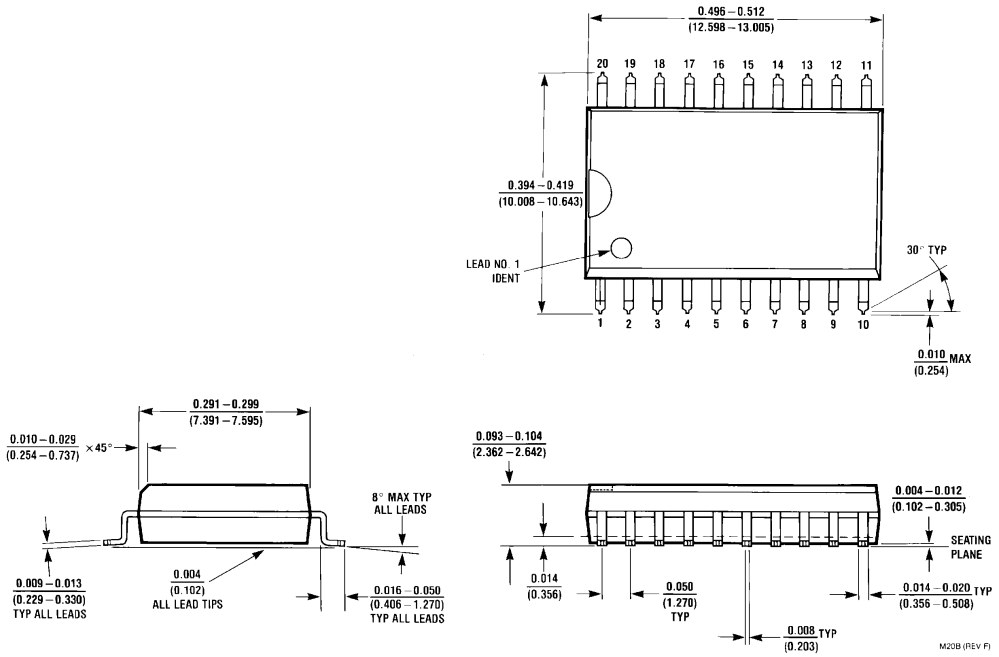
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	140		60		70		MHz
t_{PLH}	Propagation Delay	4.0	6.5	8.5	4.0	10.5	4.0	10.0	ns
t_{PHL}	CP to O_n	4.0	6.5	8.5	4.0	11.0	4.0	10.0	
t_{PZH}	Output Enable Time	2.0	9.0	11.5	2.0	14.0	2.0	12.5	ns
t_{PZL}		2.0	5.8	7.5	2.0	10.0	2.0	8.5	
t_{PHZ}	Output Disable Time	2.0	5.3	7.0	2.0	8.0	2.0	8.0	ns
t_{PLZ}		1.5	4.3	5.5	1.5	7.5	1.5	6.5	

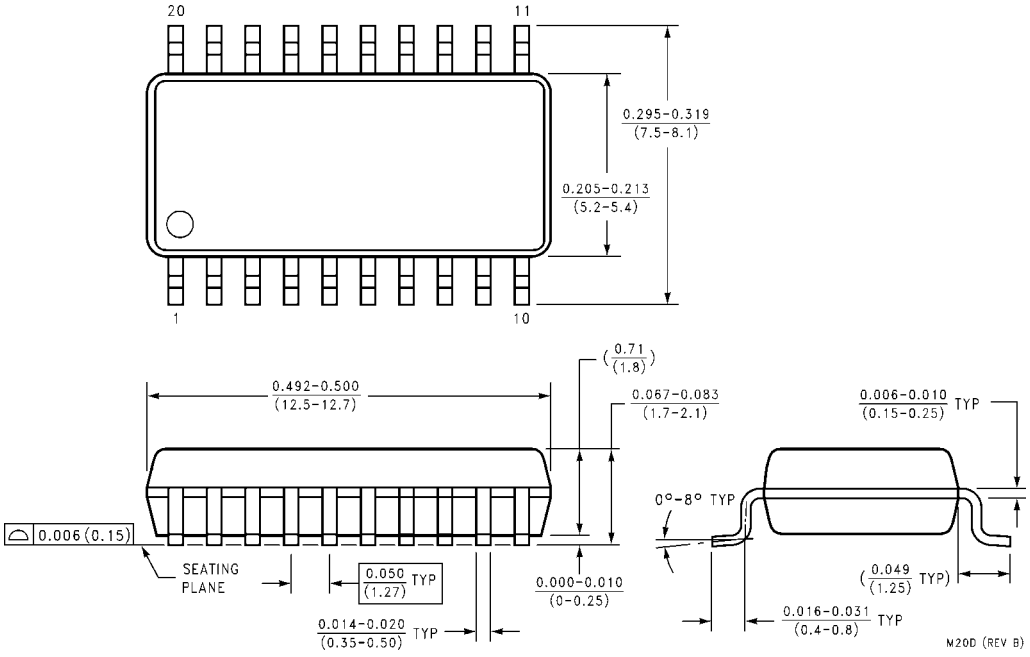
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.5		2.0		ns
$t_S(L)$	D_n to CP	2.0		2.0		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	D_n to CP	2.0		2.5		2.0		
$t_W(H)$	CP Pulse Width	7.0		7.0		7.0		ns
$t_W(L)$	HIGH or LOW	6.0		6.0		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted

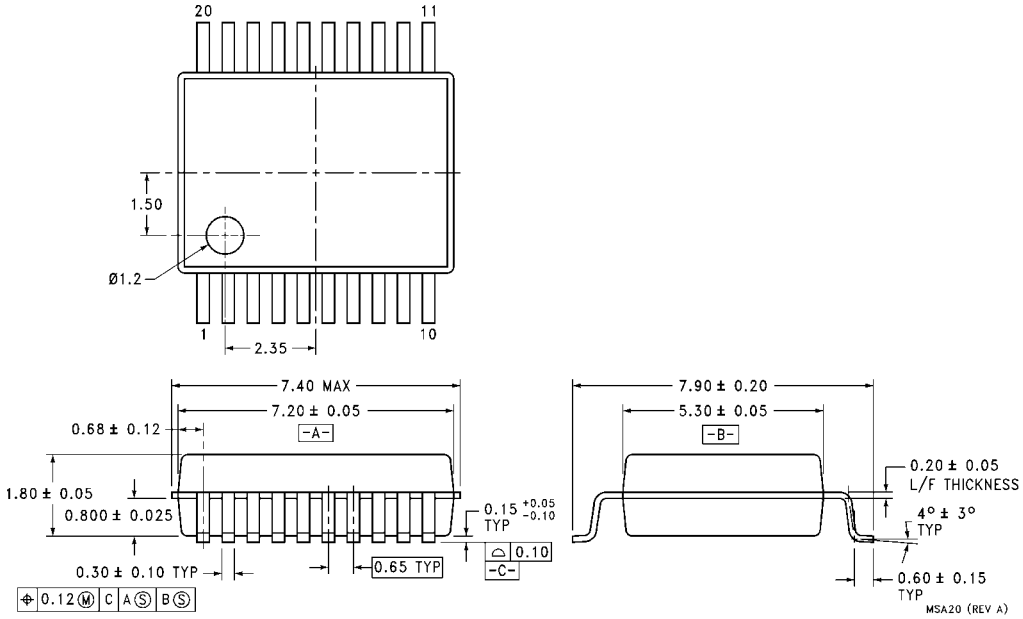


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



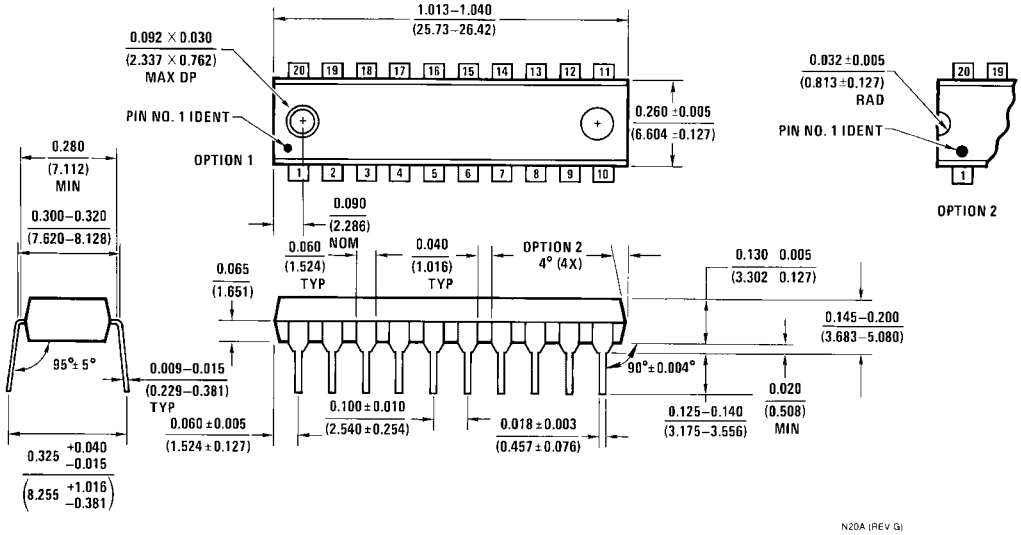
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F377
Octal D-Type Flip-Flop with Clock Enable

General Description

The 74F377 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) input loads all flip-flops simultaneously, when the Clock Enable ($\overline{CE}$) is LOW.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output. The $\overline{CE}$ input must be stable only one setup time prior to the LOW-to-HIGH clock transition for predictable operation.

Features

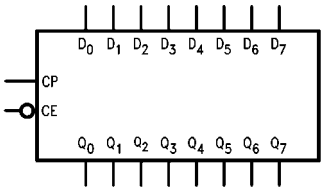
- Ideal for addressable register applications
- Clock enable for address and data synchronization applications
- Eight edge-triggered D-type flip-flops
- Buffered common clock
- See 74F273 for master reset version
- See 74F373 for transparent latch version
- See 74F374 for 3-STATE version

Ordering Code:

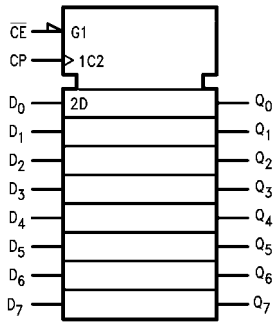
Order Number	Package Number	Package Description
74F377SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F377SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F377PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" tot he ordering code.

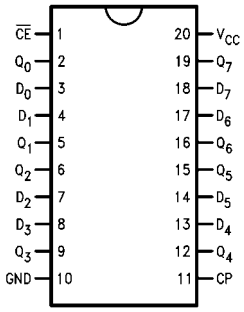
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

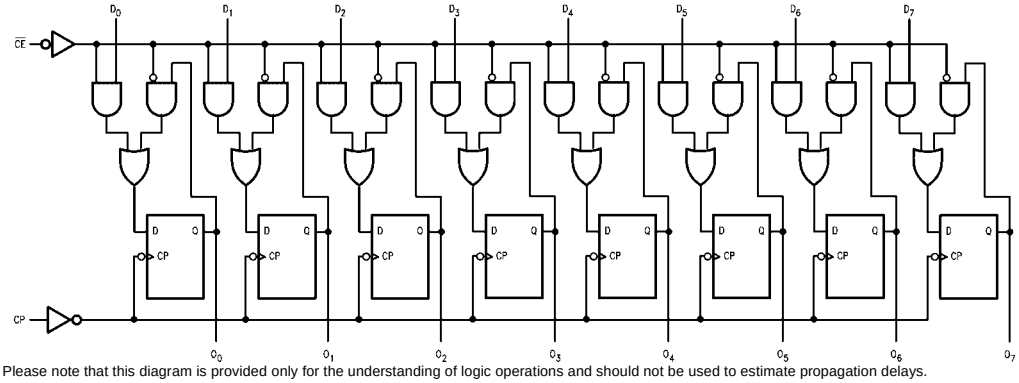
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{CE}$	Clock Enable (Active LOW)	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_7	Data Outputs	50/33.3	–1 mA/20 mA

Mode Select-Function Table

Operating Mode	Inputs			Output
	CP	$\overline{CE}$	D_n	Q_n
Load “1”	⌐	l	h	H
Load “0”	⌐	l	l	L
Hold	⌐	h	X	No Change
(Do Nothing)	X	H	X	No Change

H = HIGH Voltage Level
h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH Clock Transition
L = LOW Voltage Level
l = LOW Voltage Level one setup time prior to the LOW-to-HIGH Clock Transition
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
	Voltage							
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current				7.0	µA	Max	V_{IN} = 7.0V
	Breakdown Test							
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage		4.75			V	0.0	I_{ID} = 1.9 µA
	Test							All Other Pins Grounded
I_{OD}	Output Leakage				3.75	µA	0.0	V_{IOD} = 150 mV
	Circuit Current							All Other Pins Grounded
I_{CCH}	Power Supply Current			35	46	mA	Max	CP = ⌐
I_{CCL}				44	56			D_n = $\overline{MR}$ = HIGH

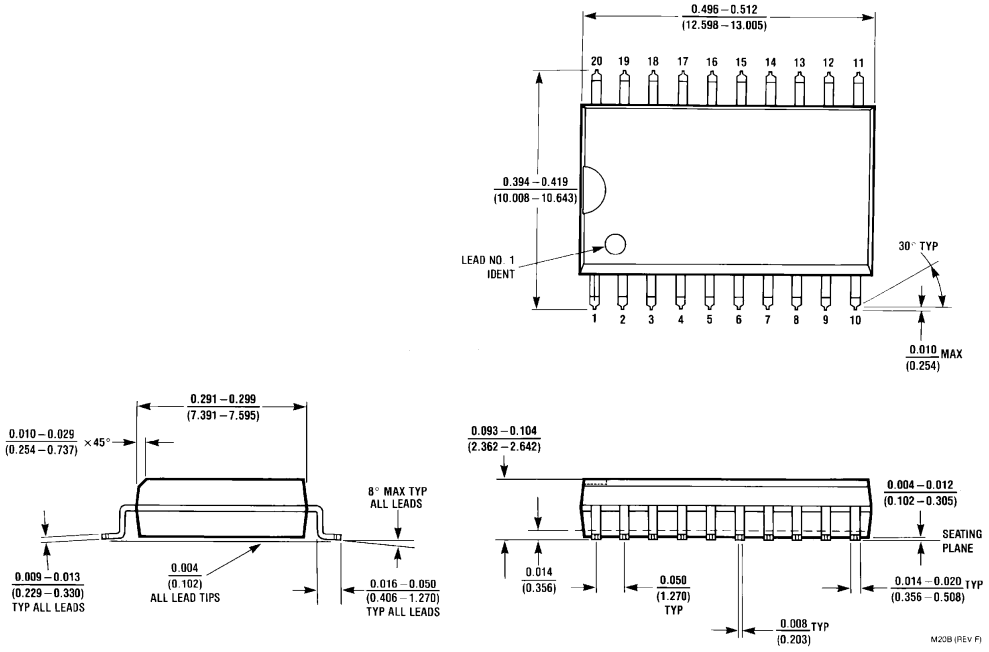
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	130			85		105		MHz
t_{PLH}	Propagation Delay	3.0		7.0	2.0	8.5	2.5	7.5	ns
t_{PHL}	CP to Q_n	4.0		9.0	3.0	10.5	3.5	9.0	

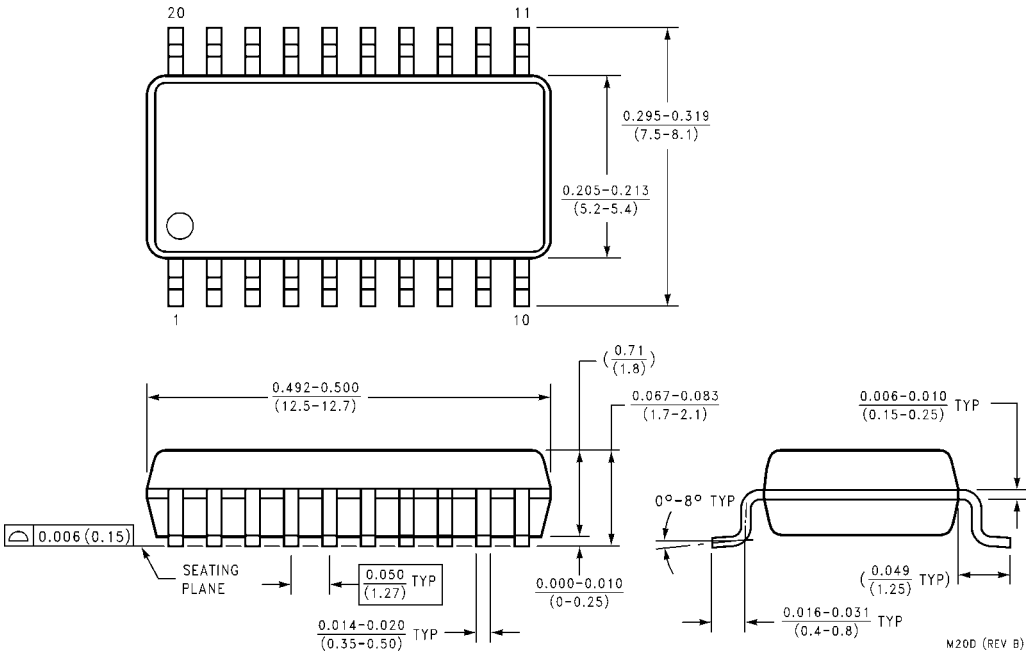
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.5		3.0		ns
$t_S(L)$	D_n to CP	3.5		4.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	0.5		1.0		0.5		ns
$t_H(L)$	D_n to CP	1.0		1.0		1.0		
$t_S(H)$	Setup Time, HIGH or LOW	4.1		4.0		4.1		ns
$t_S(L)$	$\overline{CE}$ to CP	3.5		5.0		4.0		
$t_H(H)$	Hold Time, HIGH to LOW	0.5		1.5		0.5		ns
$t_H(L)$	$\overline{CE}$ to CP	2.0		2.5		2.0		
$t_W(H)$	Clock Pulse Width,	6.0		5.0		6.0		ns
$t_W(L)$	HIGH or LOW	6.0		5.0		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted

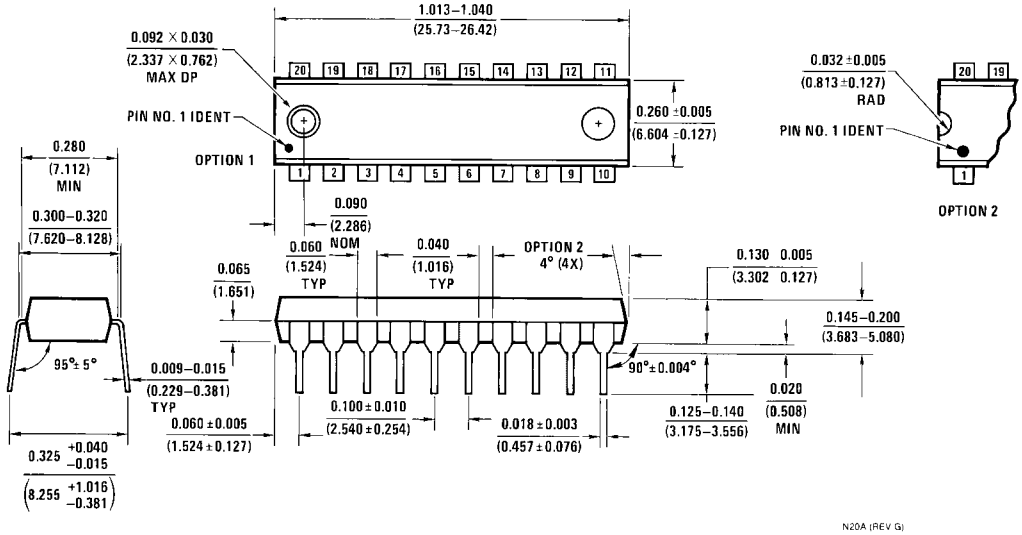


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F378
Parallel D-Type Register with Enable

General Description

The 74F378 is a 6-bit register with a buffered common Enable. This device is similar to the 74F174, but with common Enable rather than common Master Reset.

Features

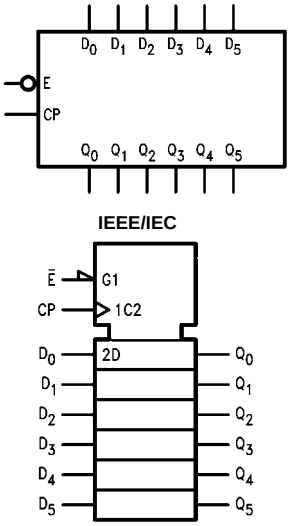
- 6-bit high-speed parallel register
- Positive edge-triggered D-type inputs
- Fully buffered common clock and enable inputs
- Input clamp diodes limit high-speed termination effects
- Full TTL and CMOS compatible

Ordering Code:

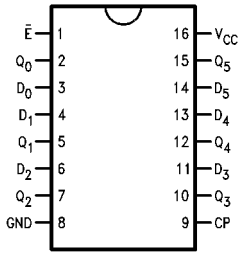
Order Number	Package Number	Package Description
74F378SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F378SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F378PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{E}$	Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
D_0–D_5	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_5	Outputs	50/33.3	–1 mA/20 mA

Functional Description

The 74F378 consists of six edge-triggered D-type flip-flops with individual D inputs and Q inputs. The Clock (CP) and Enable ($\overline{E}$) inputs are common to all flip-flops.

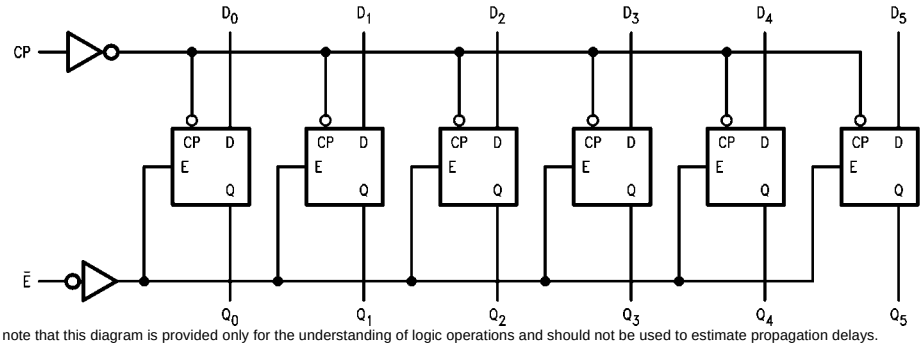
When the $\overline{E}$ input is LOW, new data is entered into the register on the LOW-to-HIGH transition of the CP input. When the $\overline{E}$ input is HIGH the register will retain the present data independent of the CP input.

Truth Table

Inputs			Output
$\overline{E}$	CP	D_n	Q_n
H	⌐	X	No Change
L	⌐	H	H
L	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCL}	Power Supply Current			30	45	mA	Max	V_O = LOW

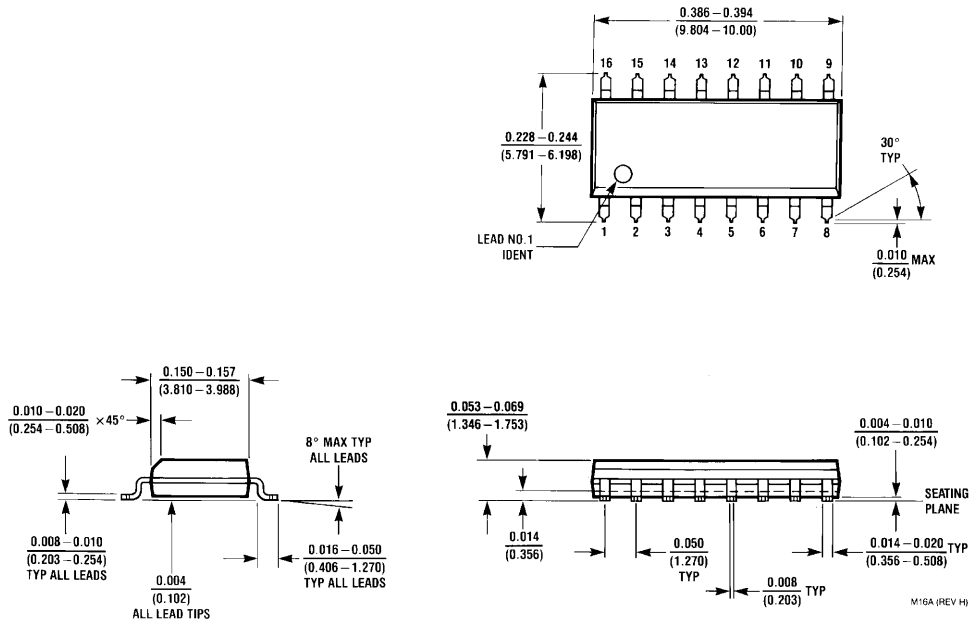
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Input Frequency	80	100		70		80		MHz
t_{PLH}	Propagation Delay	3.0	5.5	7.5	3.0	10.0	3.0	8.5	ns
t_{PHL}	CP to Q_n	3.5	6.0	8.5	3.5	10.5	3.5	9.5	

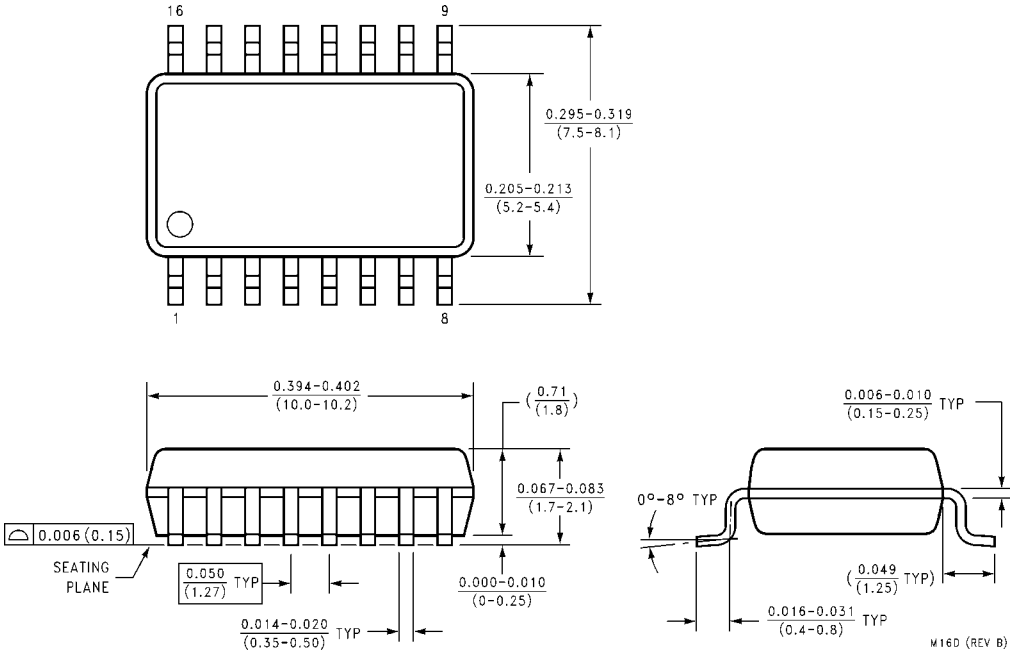
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		5.0		4.0		ns
$t_S(L)$	D_n to CP	4.0		5.0		4.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		2.0		0		
$t_H(L)$	D_n to CP	0		2.0		0		
$t_S(H)$	Setup Time, HIGH or LOW	6.0		4.5		6.0		ns
$t_S(L)$	$\overline{E}$ to CP	10.0		13.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	$\overline{E}$ to CP	0		0		0		
$t_W(H)$	CP Pulse Width	4.0		5.0		4.0		ns
$t_W(L)$	HIGH or LOW	6.0		7.5		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted

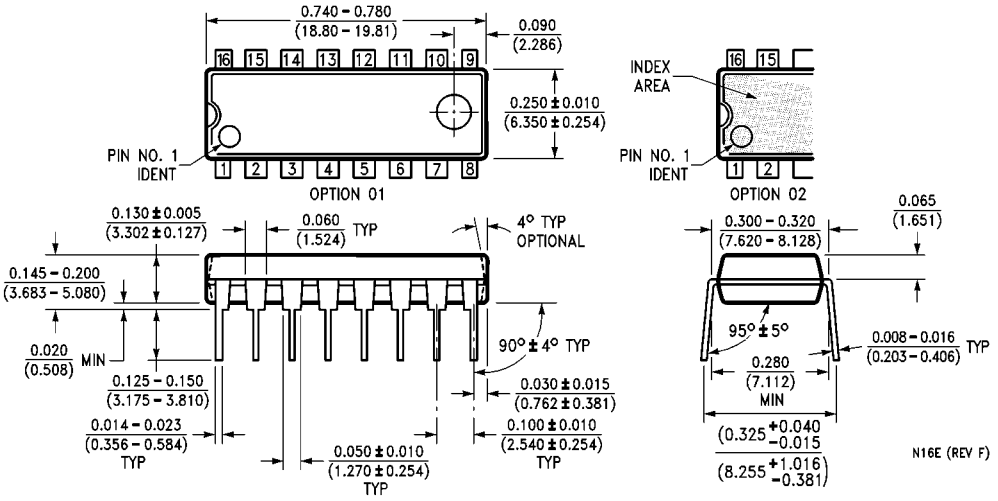


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

May 1988
Revised August 1999

74F379
Quad Parallel Register with Enable

General Description

The 74F379 is a 4-bit register with buffered common Enable. This device is similar to the 74F175 but features the common Enable rather than common Master Reset.

Features

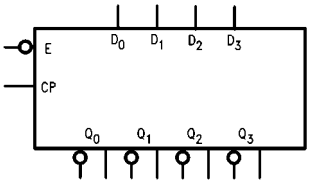
- Edge triggered D-type inputs
- Buffered positive edge-triggered clock
- Buffered common enable input
- True and complement outputs

Ordering Code:

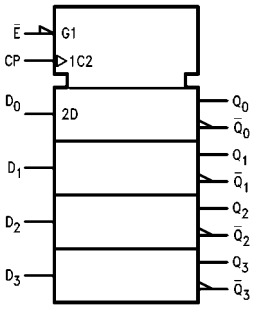
Order Number	Package Number	Package Description
74F379SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74F379SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F379PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

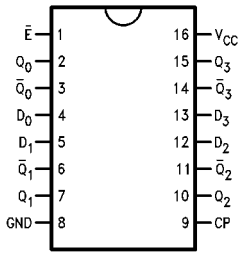
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{E}$	Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
D_0–D_3	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
Q_0–Q_3	Flip-Flop Outputs	50/33.3	–1 mA/20 mA
$\overline{Q}_0$–$\overline{Q}_3$	Complement Outputs	50/33.3	–1 mA/20 mA

Functional Description

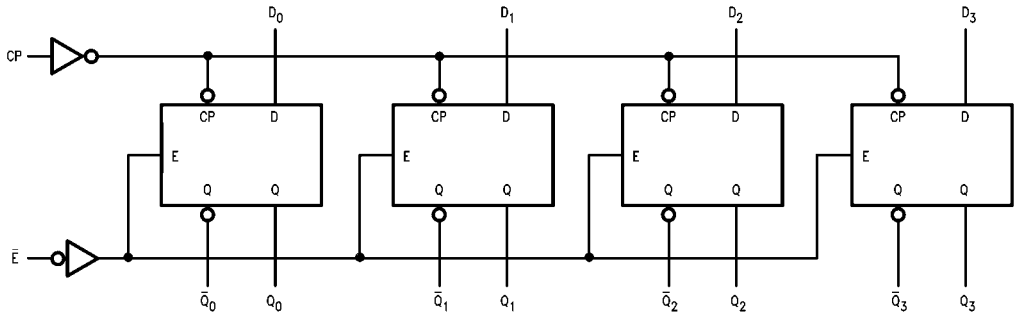
The 74F379 consists of four edge-triggered D-type flip-flops with individual D inputs and Q and $\overline{Q}$ outputs. The Clock (CP) and Enable ($\overline{E}$) inputs are common to all flip-flops. When the $\overline{E}$ is input HIGH, the register will retain the present data independent of the CP input. The D_n and $\overline{E}$ inputs can change when the clock is in either state, provided that the recommended setup and hold times are observed.

Truth Table

Inputs			Outputs	
$\overline{E}$	CP	D_n	Q_n	$\overline{Q}_n$
H	⌐	X	NC	NC
L	⌐	H	H	L
L	⌐	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
	Voltage							
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCL}	Power Supply Current			28	40	mA	Max	V_O = LOW

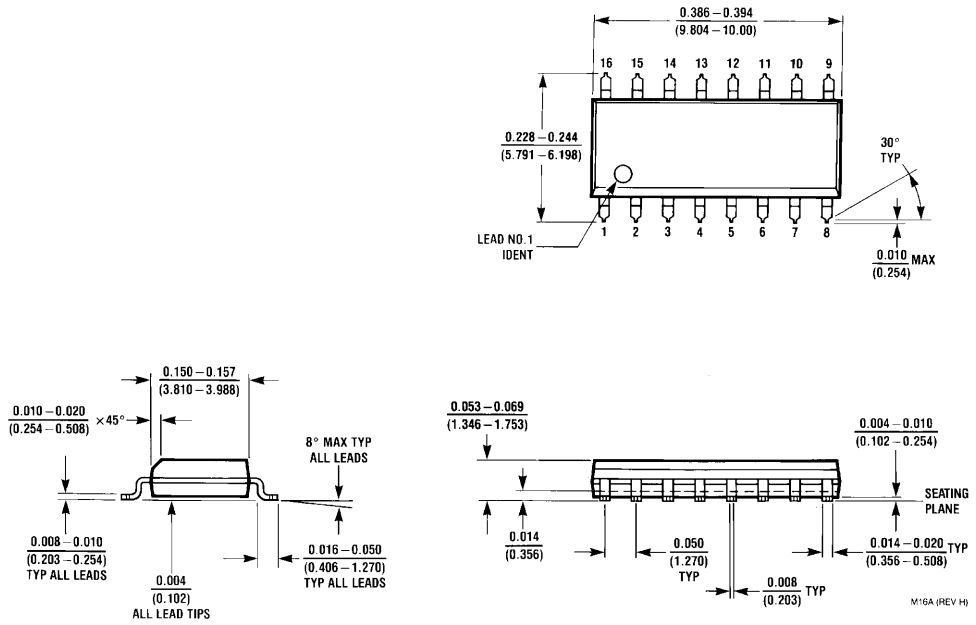
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	140		75		100		MHz
t_{PLH}	Propagation Delay	3.5	5.0	6.5	3.0	8.5	3.5	7.5	ns
t_{PHL}	CP to Q_n, $\overline{Q}_n$	5.0	6.5	8.5	4.0	10.0	5.0	9.5	

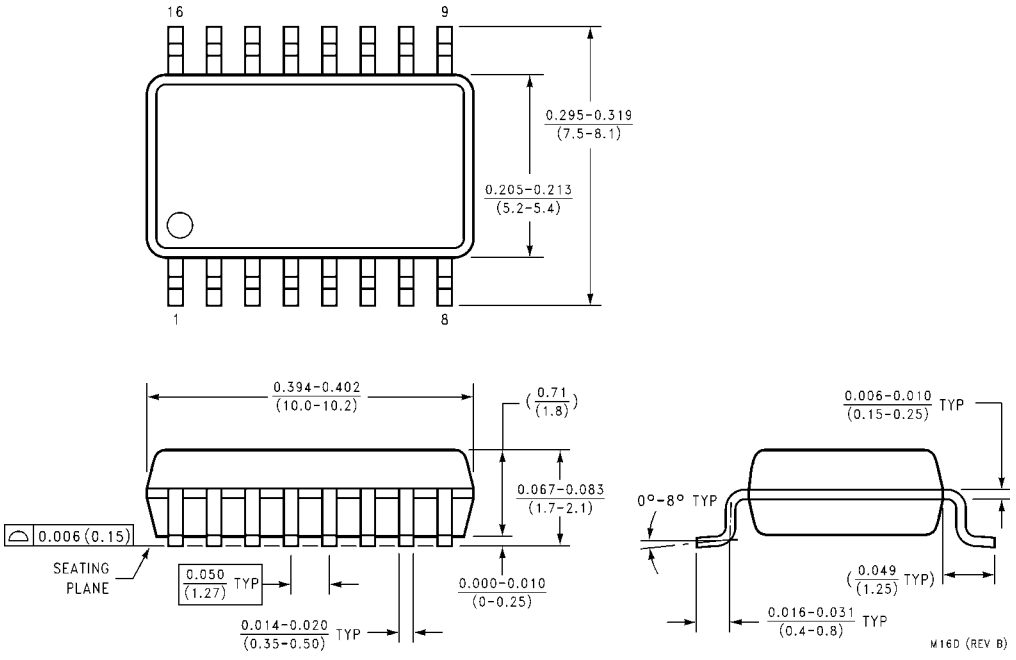
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		4.0			3.0	ns
$t_S(L)$	D_n to CP	3.0		4.0			3.0	
$t_H(H)$	Hold Time, HIGH or LOW	1.0		2.0			1.0	
$t_H(L)$	D_n to CP	1.0		2.0			1.0	
$t_S(H)$	Setup Time, HIGH or LOW	6.0		8.0			6.0	ns
$t_S(L)$	$\overline{E}$ to CP	6.0		8.0			6.0	
$t_H(H)$	Hold Time, HIGH or LOW	0		0			0	
$t_H(L)$	$\overline{E}$ to CP	0		0			0	
$t_W(H)$	CP Pulse Width	4.0		5.0			4.0	ns
$t_W(L)$	HIGH or LOW	5.0		7.0			5.0	

Physical Dimensions inches (millimeters) unless otherwise noted

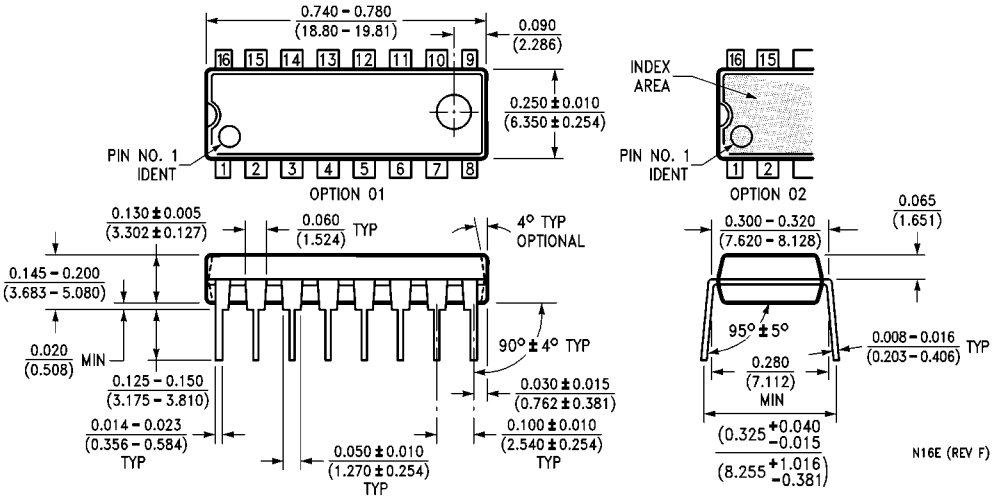


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised November 1999

74F38
Quad Two-Input NAND Buffer (Open Collector)

General Description

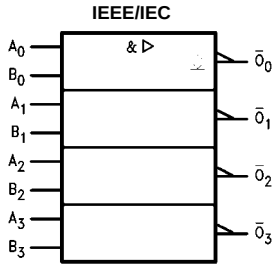
This device contains four independent gates, each of which performs the logic NAND function. The open-collector outputs require external pull-up resistors for proper logical operation.

Ordering Code:

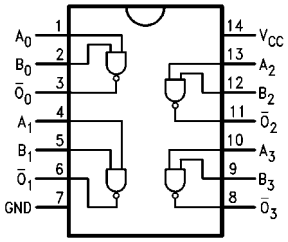
Order Number	Package Number	Package Description
74F38SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F38SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F38PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/2.0	20 µA/–1.2 mA
$\overline{O}_n$	Outputs	OC (Note 1) /106.6	OC (Note 1) /64 mA

Note 1: OC = Open Collector

Function Table

Inputs		Output
A	B	$\overline{O}$
L	L	H
L	H	H
H	L	H
H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

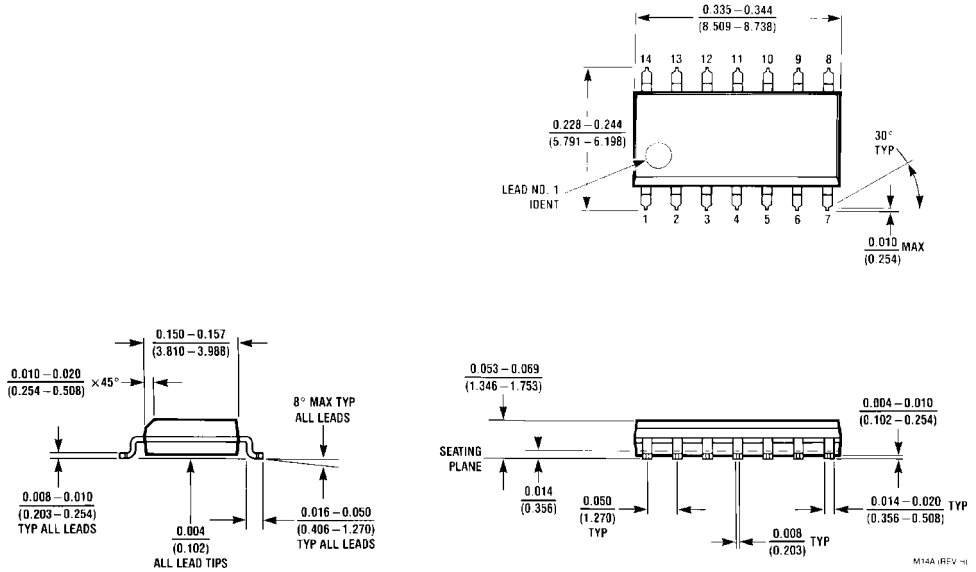
DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OL}	Output LOW 10% V_{CC} Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−1.2	mA	Max	V_{IN} = 0.5V
I_{OHC}	Open Collector, Output OFF Leakage Test			250	µA	Min	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current		2.1	7.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		26.0	30.0	mA	Max	V_O = LOW

AC Electrical Characteristics

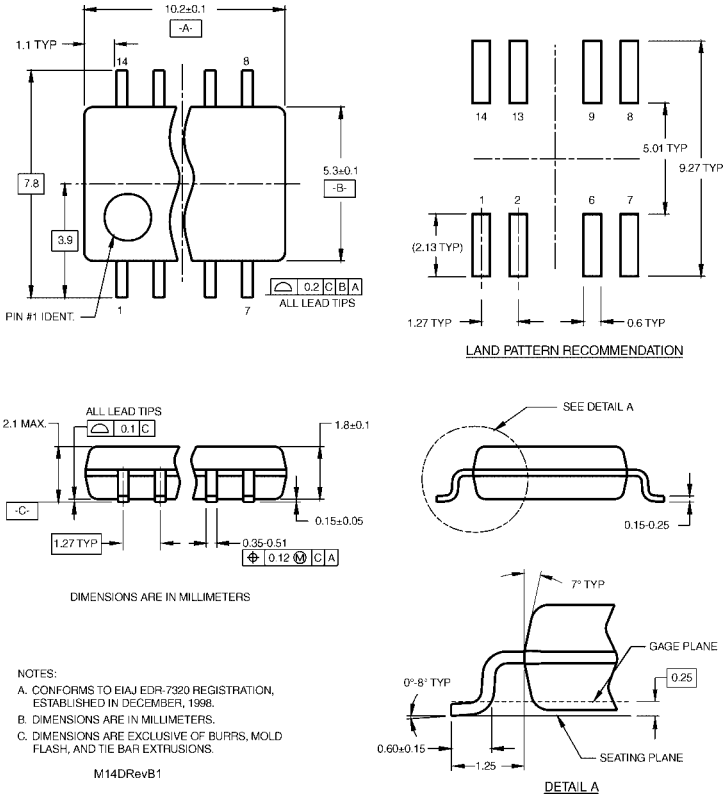
Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	6.5	9.7	12.5	6.5	13.0	ns
t_{PHL}	A_n, B_n to $\overline{O}_n$	1.5	2.1	5.0	1.5	5.5	

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

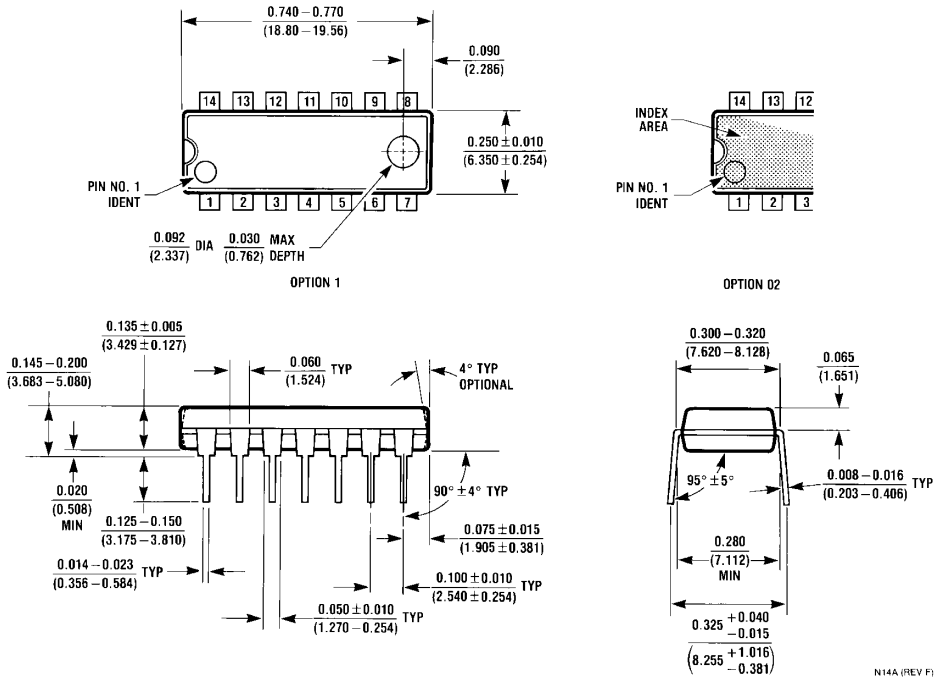
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

May 1988
Revised August 1999

74F381
4-Bit Arithmetic Logic Unit

General Description

The 74F381 performs three arithmetic and three logic operations on two 4-bit words, A and B. Two additional select input codes force the function outputs LOW or HIGH. Carry propagate and generate outputs are provided for use with the 74F182 carry lookahead generator for high-speed expansion to longer word lengths. For ripple expansion, refer to the 74F382 ALU data sheet.

Features

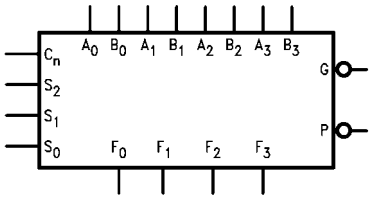
- Low input loading minimizes drive requirements
- Performs six arithmetic and logic functions
- Selectable LOW (clear) and HIGH (preset) functions
- Carry generate and propagate outputs for use with carry lookahead generator

Ordering Code:

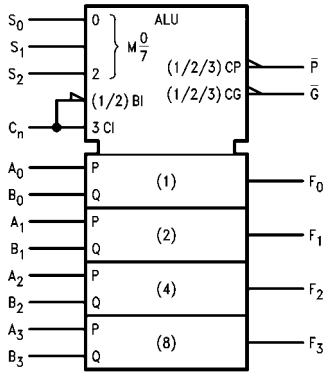
Order Number	Package Number	Package Description
74F381SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F381SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F381PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

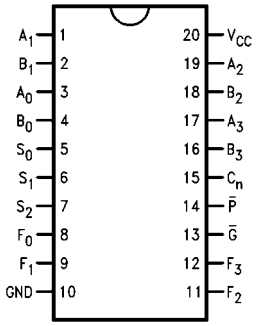
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	A Operand Inputs	1.0/3.0	20 µA/–1.8 mA
B_0–B_3	B Operand Inputs	1.0/3.0	20 µA/–1.8 mA
S_0–S_2	Function Select Inputs	1.0/1.0	20 µA/–0.6 mA
C_n	Carry Input	1.0/4.0	20 µA/–2.4 mA
$\overline{G}$	Carry Generate Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{P}$	Carry Propagate Output (Active LOW)	50/33.3	–1 mA/20 mA
F_0–F_3	Function Outputs	50/33.3	–1 mA/20 mA

Functional Description

Signals applied to the Select inputs S_0–S_2 determine the mode of operation, as indicated in the Function Select Table. An extensive listing of input and output levels is shown in the Truth Table. The circuit performs the arithmetic functions for either active HIGH or active LOW operands, with output levels in the same convention. In the Subtract operating modes, it is necessary to force a carry (HIGH for active HIGH operands, LOW for active LOW operands) into the C_n input of the least significant package.

The Carry Generate ($\overline{G}$) and Carry Propagate ($\overline{P}$) outputs supply input signals to the 74F182 carry lookahead generator for expansion to longer word length, as shown in Figure 2. Note that an 74F382 ALU is used for the most significant package. Typical delays for Figure 2 are given in Figure 1.

Function Select Table

Select S_0	Select S_1	Select S_2	Operation
L	L	L	Clear
H	L	L	B Minus A
L	H	L	A Minus B
H	H	L	A Plus B
L	L	H	A⊕B
H	L	H	A + B
L	H	H	AB
H	H	H	Preset

H = HIGH Voltage Level
L = LOW Voltage Level

Path Segment	Toward F	Output $C_n + 4$, OVR
A_i or B_i to $\overline{P}$	7.2 ns	7.2 ns
$\overline{P}_i$ to C_n + ('F182)	6.2 ns	6.2 ns
C_n to F	8.1 ns	—
C_n or $C_n + 4$, OVR	—	8.0 ns
Total Delay	21.5 ns	21.4 ns

FIGURE 1. 16-Bit Delay Tabulation

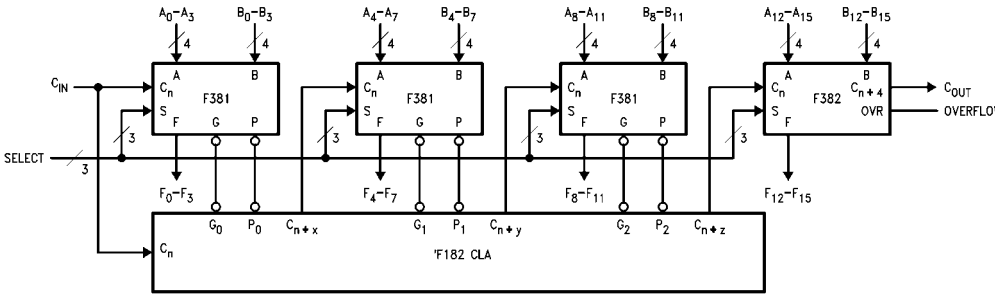


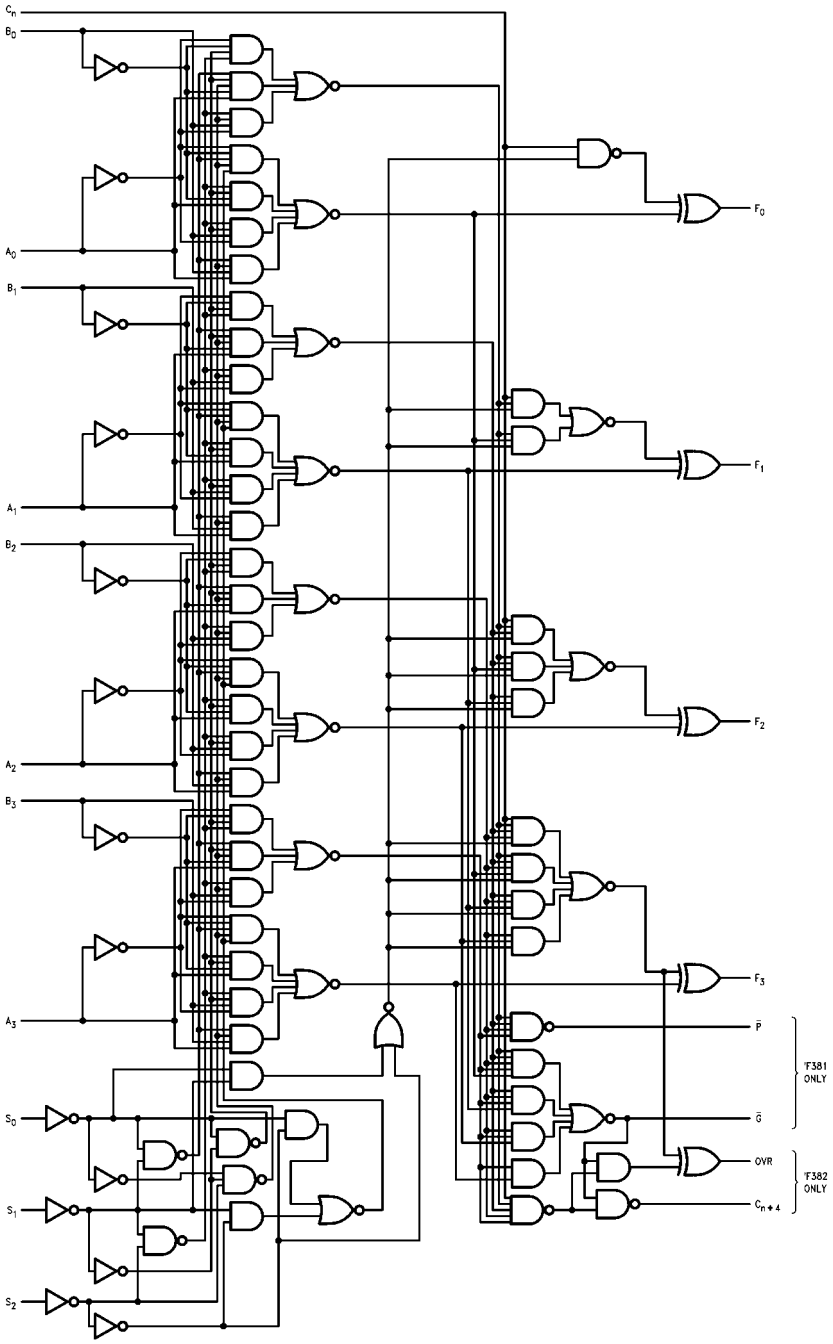
FIGURE 2. 16-Bit Lookahead Carry ALU Expansion

Truth Table

	Inputs						Outputs					
Function	S_0	S_1	S_2	C_n	A_n	B_n	F_0	F_1	F_2	F_3	$\overline{G}$	$\overline{P}$
CLEAR	L	L	L	X	X	X	L	L	L	L	L	L
B Minus A	H	L	L	L	L	L	H	H	H	H	H	L
				L	L	H	L	H	H	H	L	L
				L	H	L	L	L	L	L	H	H
				L	H	H	H	H	H	H	H	L
				H	L	L	L	L	L	L	H	L
				H	L	H	H	H	H	H	L	L
				H	H	L	H	L	L	L	H	H
				H	H	H	L	L	L	L	H	L
A Minus B	L	H	L	L	L	L	H	H	H	H	H	L
				L	L	H	L	L	L	L	H	H
				L	H	L	L	H	H	H	L	L
				L	H	H	H	H	H	H	H	L
				H	L	L	L	L	L	L	H	L
				H	L	H	H	L	L	L	H	H
				H	H	L	H	H	H	H	L	L
				H	H	H	L	L	L	L	H	L
A Plus B	H	H	L	L	L	L	L	L	L	L	H	H
				L	L	H	H	H	H	H	H	L
				L	H	L	H	H	H	H	H	L
				L	H	H	L	H	H	H	L	L
				H	L	L	H	L	L	L	H	H
				H	L	H	L	L	L	L	H	L
				H	H	L	L	L	L	L	H	L
				H	H	H	H	H	H	H	L	L
A ⊕ B	L	L	H	X	L	L	L	L	L	L	H	H
				X	L	H	H	H	H	H	H	H
				X	H	L	H	H	H	H	H	L
				X	H	H	L	L	L	L	L	L
A + B	H	L	H	X	L	L	L	L	L	L	H	H
				X	L	H	H	H	H	H	H	H
				X	H	L	H	H	H	H	H	H
				X	H	H	H	H	H	H	H	L
AB	L	H	H	X	L	L	L	L	L	L	L	L
				X	L	H	L	L	L	L	H	H
				X	H	L	L	L	L	L	L	L
				X	H	H	H	H	H	H	H	L
PRESET	H	H	H	X	L	L	H	H	H	H	H	H
				X	L	H	H	H	H	H	H	H
				X	H	L	H	H	H	H	H	H
				X	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

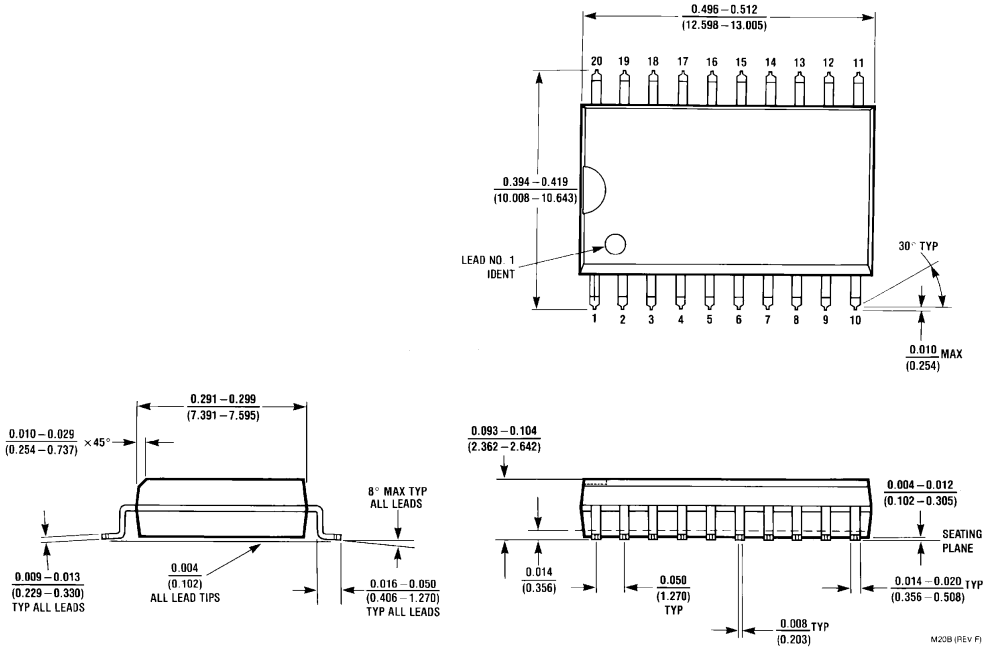
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA		V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (S_n)
					−1.8	mA	Max	V_{IN} = 0.5V (A_n, B_n)
					−2.4	mA	Max	V_{IN} = 0.5V (C_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			59	89	mA	Max	

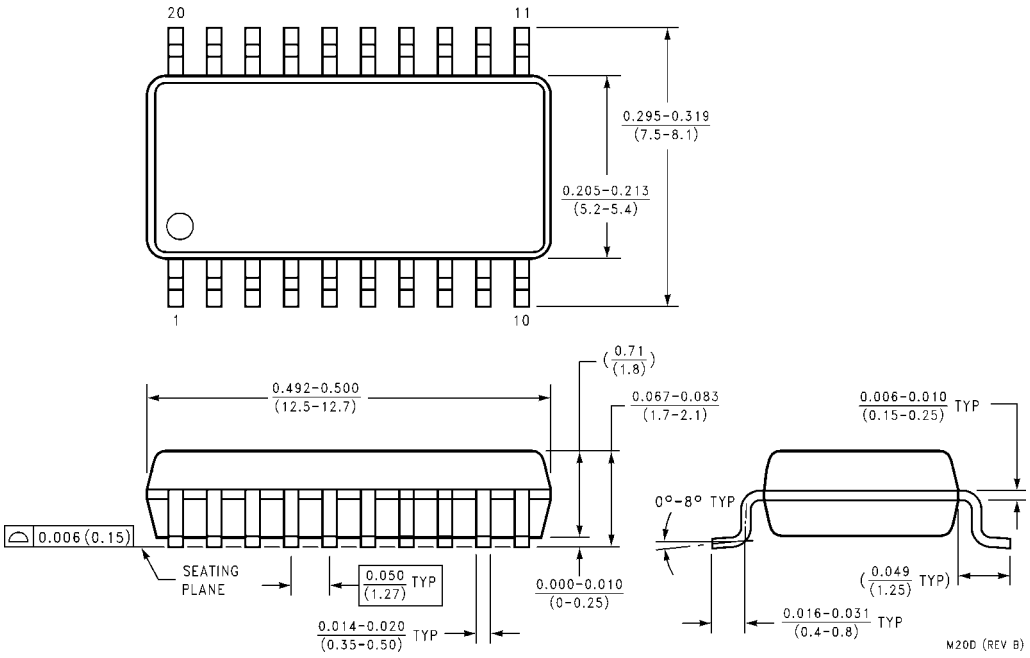
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	8.1	12.0	2.5	13.0	ns
t_{PHL}	C_n to F_i	2.5	5.7	8.0	2.5	9.0	
t_{PLH}	Propagation Delay	4.0	10.4	15.0	4.0	16.0	ns
t_{PHL}	Any A or B to Any F	3.5	8.2	11.0	3.5	12.0	
t_{PLH}	Propagation Delay	4.5	8.3	20.5	4.5	21.5	ns
t_{PHL}	S_i to F_i	4.0	8.2	15.0	4.0	16.0	
t_{PLH}	Propagation Delay	3.5	6.4	10.0	3.5	11.0	ns
t_{PHL}	A_i or B_i to $\overline{G}$	3.5	6.8	10.0	3.0	11.0	
t_{PLH}	Propagation Delay	2.5	7.2	10.5	2.5	11.5	ns
t_{PHL}	A_i or B_i to $\overline{P}$	3.5	6.5	9.5	3.5	10.5	
t_{PLH}	Propagation Delay	4.0	7.8	12.0	4.0	13.0	ns
t_{PHL}	S_i to $\overline{G}$ or $\overline{P}$	4.5	10.2	13.5	4.5	14.5	

Physical Dimensions inches (millimeters) unless otherwise noted

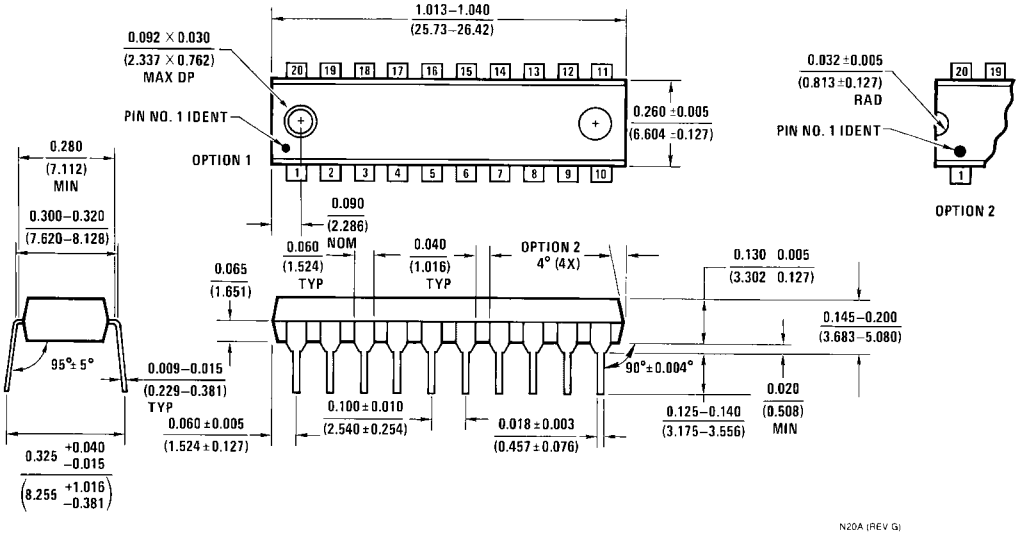


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR TM

May 1988
Revised August 1999

74F382
4-Bit Arithmetic Logic Unit

General Description

The 74F382 performs three arithmetic and three logic operations on two 4-bit words, A and B. Two additional Select input codes force the Function outputs LOW or HIGH. An Overflow output is provided for convenience in twos complement arithmetic. A Carry output is provided for ripple expansion. For high-speed expansion using a Carry Lookahead Generator, refer to the 74F381 data sheet.

Features

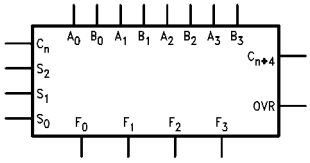
- Performs six arithmetic and logic functions
- Selectable LOW (clear) and HIGH (preset) functions
- LOW input loading minimizes drive requirements
- Carry output for ripple expansion
- Overflow output for twos complement arithmetic

Ordering Code:

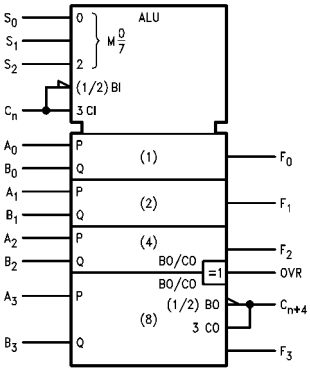
Order Number	Package Number	Package Description
74F382SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F382SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F382PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

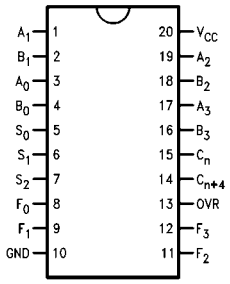
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	A Operand Inputs	1.0/4.0	20 µA/–2.4 mA
B_0–B_3	B Operand Inputs	1.0/4.0	20 µA/–2.4 mA
S_0–S_2	Function Select Inputs	1.0/1.0	20 µA/–0.6 mA
C_n	Carry Input	1.0/5.0	20 µA/–3.0 mA
C_{n+4}	Carry Output	50/33.3	–1 mA/20 mA
OVR	Overflow Output	50/33.3	–1 mA/20 mA
F_0–F_3	Function Outputs	50/33.3	–1 mA/20 mA

Functional Description

Signals applied to the Select inputs S_0–S_2 determine the mode of operation, as indicated in the Function Select Table. An extensive listing of input and output levels is shown in the Truth Table. The circuit performs the arithmetic functions for either active HIGH or active LOW operands, with output levels in the same convention. In the Subtract operating modes, it is necessary to force a carry (HIGH for active HIGH operands, LOW for active LOW operands) into the C_n input of the least significant package. Ripple expansion is illustrated in Figure 2. The overflow output OVR is the Exclusive-OR of C_{n+3} and C_{n+4}; a HIGH signal on OVR indicates overflow in twos complement operation. Typical delays for Figure 2 are given in Figure 1.

Function Select Table

Select			Operation
S_0	S_1	S_2	
L	L	L	Clear
H	L	L	B Minus A
L	H	L	A Minus B
H	H	L	A Plus B
L	L	H	A ⊕ B
H	L	H	A + B
L	H	H	AB
H	H	H	Preset

H = HIGH Voltage Level
L = LOW Voltage Level

Path Segment	Toward F	Output C_{n+4}, OVR
A_1 or B_1 to C_{n+4}	6.5 ns	6.5 ns
C_n to C_{n+4}	6.3 ns	6.3 ns
C_n to C_{n+4}	6.3 ns	6.3 ns
C_n to F	8.1 ns	—
C_n to C_{n+4}, OVR	—	8.0 ns
Total Delay	27.2 ns	27.1 ns

FIGURE 1. 16-Bit Delay Tabulation

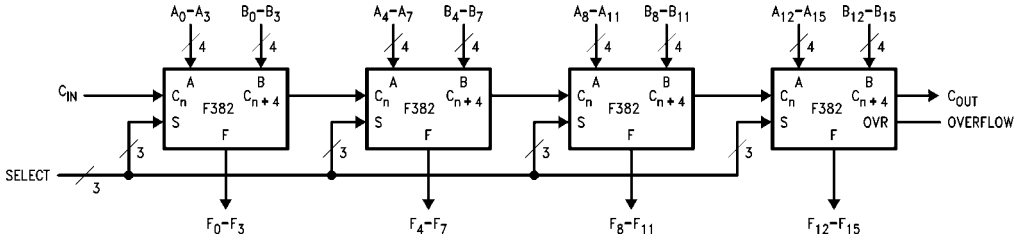


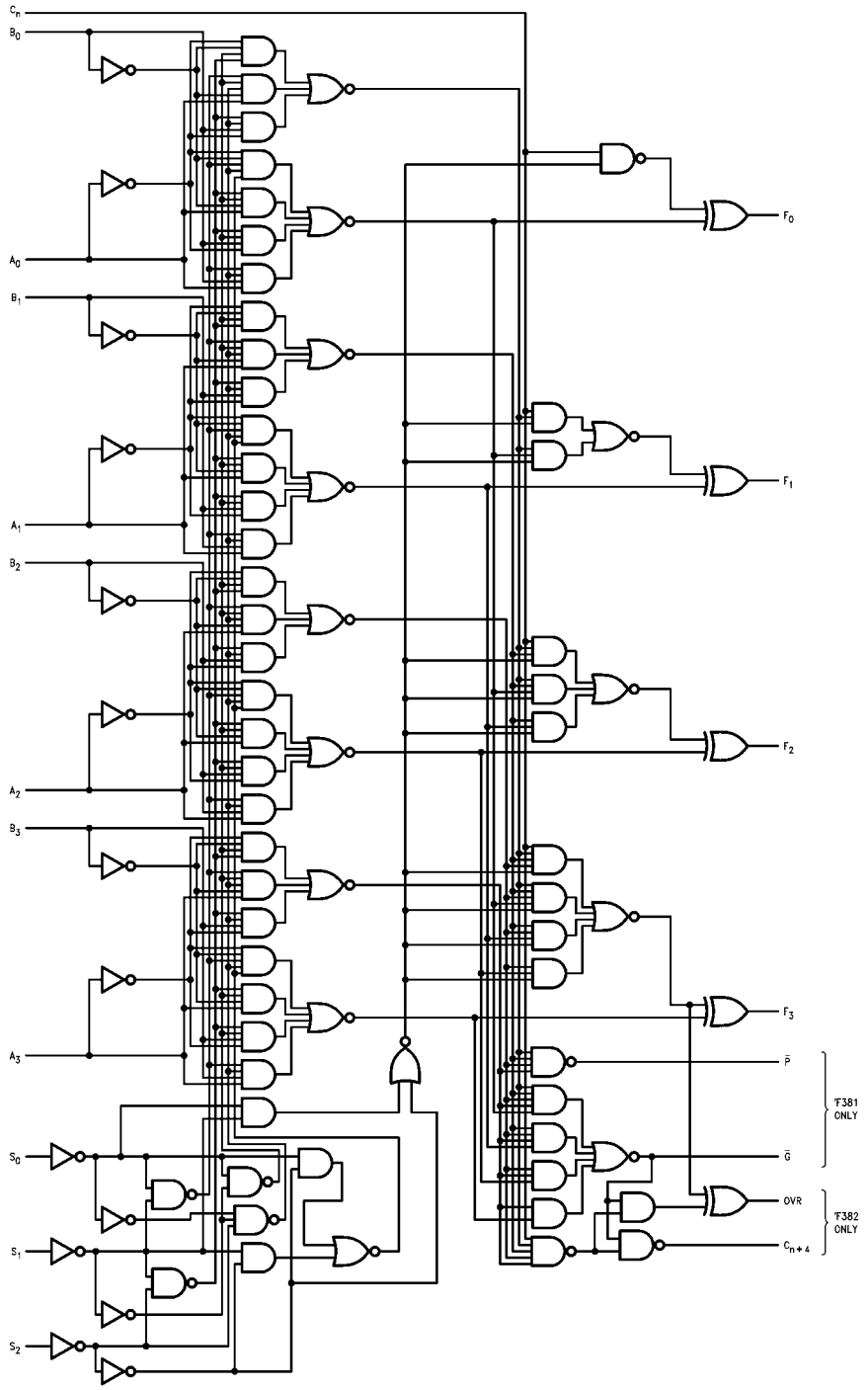
FIGURE 2. 16-Bit Ripply Carry ALU Expansion

Truth Table

	Inputs						Outputs					
Function	S_0	S_1	S_2	C_n	A_n	B_n	F_0	F_1	F_2	F_3	**OVR**	C_{n+4}
CLEAR	L	L	L	L	X	X	L	L	L	L	H	H
				H	X	X	L	L	L	L	H	H
B MINUS A	H	L	L	L	L	L	H	H	H	H	L	L
				L	L	H	L	H	H	H	L	H
				L	H	L	L	L	L	L	L	L
				L	H	H	H	H	H	H	L	L
				H	L	L	L	L	L	L	L	H
				H	L	H	H	H	H	H	L	H
				H	H	L	H	L	L	L	L	L
				H	H	H	L	L	L	L	L	H
A MINUS B	L	H	L	L	L	L	H	H	H	H	L	L
				L	L	H	L	L	L	L	L	L
				L	H	L	L	H	H	H	L	H
				L	H	H	H	H	H	H	L	L
				H	L	L	L	L	L	L	L	H
				H	L	H	H	L	L	L	L	L
				H	H	L	H	H	H	H	L	H
				H	H	H	L	L	L	L	L	H
A PLUS B	H	H	L	L	L	L	L	L	L	L	L	L
				L	L	H	H	H	H	H	L	L
				L	H	L	H	H	H	H	L	L
				L	H	H	L	H	H	H	L	H
				H	L	L	H	L	L	L	L	L
				H	L	H	L	L	L	L	L	H
				H	H	L	L	L	L	L	L	H
				H	H	H	H	H	H	H	L	H
A ⊕ B	L	L	H	X	L	L	L	L	L	L	L	L
				X	L	H	H	H	H	H	L	L
				L	H	L	H	H	H	H	L	L
				X	H	H	L	L	L	L	H	H
				H	H	L	H	H	H	H	H	H
A + B	H	L	H	X	L	L	L	L	L	L	L	L
				X	L	H	H	H	H	H	L	L
				X	H	L	H	H	H	H	L	L
				L	H	H	H	H	H	H	L	L
				H	H	H	H	H	H	H	H	H
AB	L	H	H	X	L	L	L	L	L	L	H	H
				X	L	H	L	L	L	L	L	L
				X	H	L	L	L	L	L	H	H
				L	H	H	H	H	H	H	L	L
				H	H	H	H	H	H	H	H	H
PRESET	H	H	H	X	L	L	H	H	H	H	L	L
				X	L	H	H	H	H	H	L	L
				X	H	L	H	H	H	H	L	L
				L	H	H	H	H	H	H	L	L
				H	H	H	H	H	H	H	H	H

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

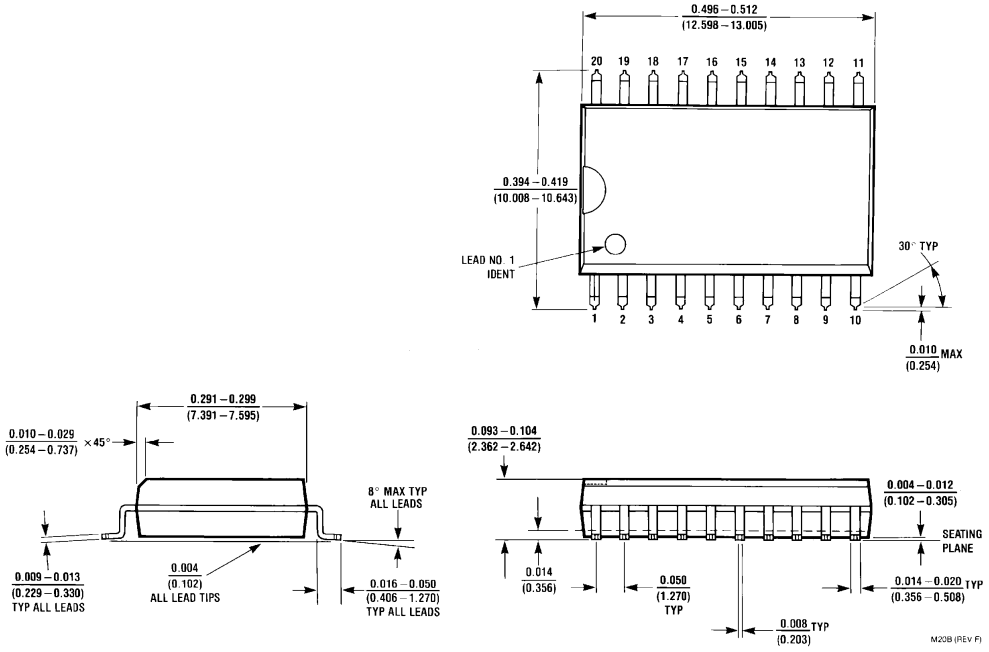
DC Electrical Characteristics over Operating Temperature Range unless otherwise specified

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (S_0 – S_2)
					−2.4			V_{IN} = 0.5V (A_0 – A_3, B_0 – B_3)
					−3.0			V_{IN} = 0.5V (C_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			54	81	mA	Max	

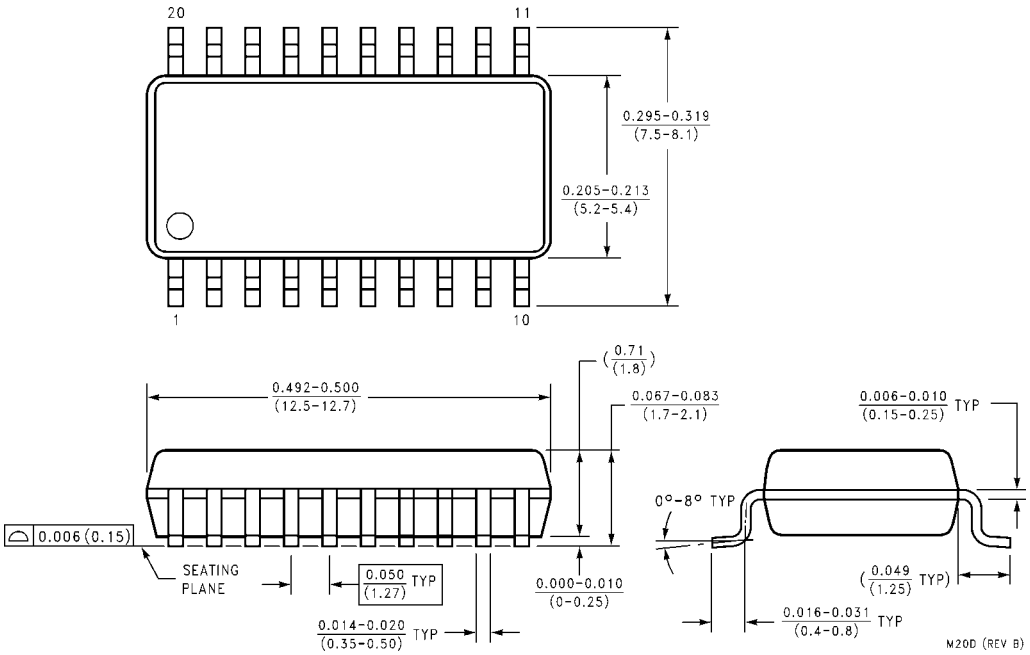
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	8.1	12.0	3.0	13.0	ns
t_{PHL}	C_n to F_i	2.5	5.7	8.0	2.5	9.0	
t_{PLH}	Propagation Delay	4.0	10.4	15.0	3.5	17.0	ns
t_{PHL}	Any A or B to Any F	3.0	8.2	11.0	2.5	12.0	
t_{PLH}	Propagation Delay	6.5	11.0	20.5	5.5	21.5	ns
t_{PHL}	S_i to F_i	4.0	8.2	15.0	4.0	17.5	
t_{PLH}	Propagation Delay	3.5	6.0	8.5	3.5	11.0	ns
t_{PHL}	A_i or B_i to $C_n + 4$	3.5	6.5	9.0	3.5	10.5	
t_{PLH}	Propagation Delay	7.0	12.5	16.5	7.0	17.5	ns
t_{PHL}	S_i to OVR or C_{n+4}	5.0	9.0	12.0	5.0	14.5	
t_{PLH}	Propagation Delay	2.5	5.6	8.0	2.0	9.0	ns
t_{PHL}	C_n to C_{n+4}	3.5	6.3	9.0	2.0	10.0	
t_{PLH}	Propagation Delay	3.5	8.0	11.0	3.5	13.0	ns
t_{PHL}	C_n to OVR	2.5	7.1	10.0	2.5	11.0	
t_{PLH}	Propagation Delay	7.0	11.5	15.5	7.0	16.5	ns
t_{PHL}	A_i or B_i to OVR	3.0	8.0	10.5	3.0	11.5	

Physical Dimensions inches (millimeters) unless otherwise noted

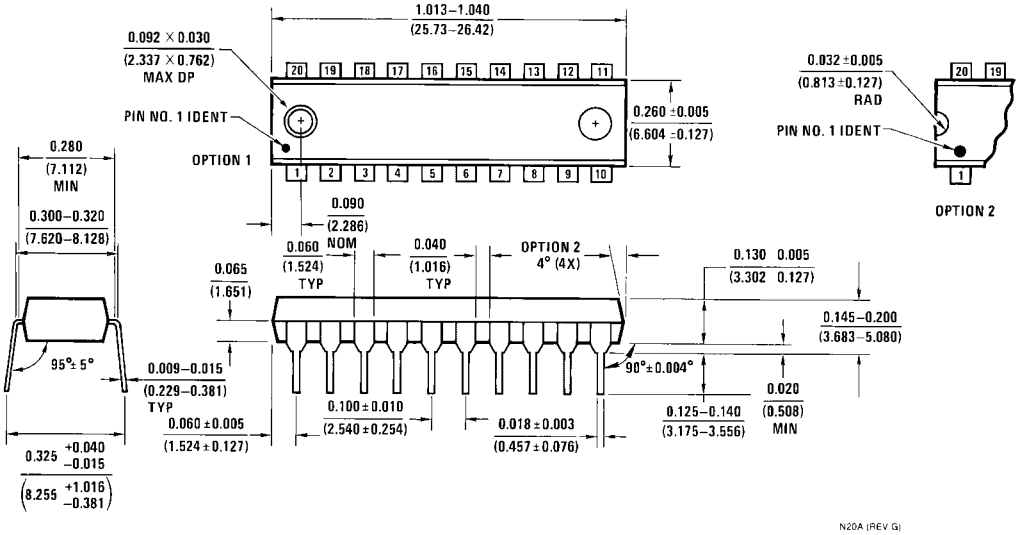


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F398 • 74F399
Quad 2-Port Register

General Description

The 74F398 and 74F399 are the logical equivalents of a quad 2-input multiplexer feeding into four edge-triggered flip-flops. A common Select input determines which of the two 4-bit words is accepted. The selected data enters the flip-flops on the rising edge of the clock. The 74F399 is the 16-pin version of the 74F398, with only the Q outputs of the flip-flops available.

Features

- Select inputs from two data sources
- Fully positive edge-triggered operation
- Both true and complement outputs—74F398

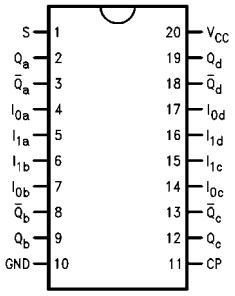
Ordering Code:

Order Number	Package Number	Package Description
74F398SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74F398PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74F399SC	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
74F399SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F399PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

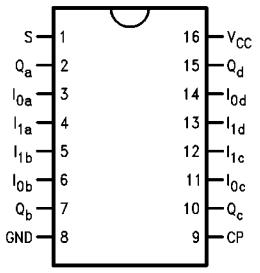
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagrams

74F398

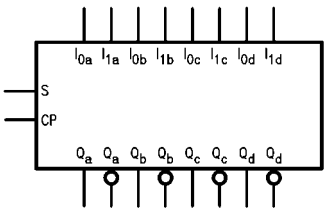


74F399

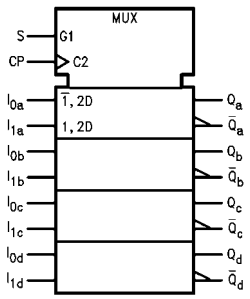


Logic Symbols

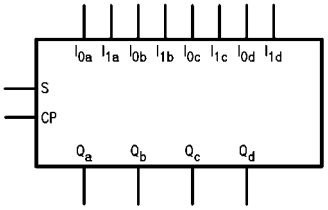
74F398



74F398

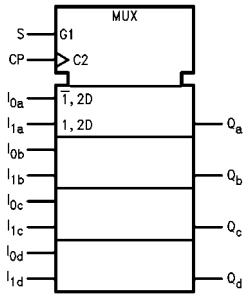


74F399



IEEE/IEC

74F399



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S	Common Select Input	1.0/1.0	20 µA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
I_{0a}–I_{0d}	Data Inputs from Source 0	1.0/1.0	20 µA/–0.6 mA
I_{1a}–I_{1d}	Data Inputs from Source 1	1.0/1.0	20 µA/–0.6 mA
Q_a–Q_d	Register True Outputs	50/33.3	–1 mA/20 mA
$\overline{Q}_a$–$\overline{Q}_d$	Register Complementary Outputs (74F398)	50/33.3	–1 mA/20 mA

Functional Description

The 74F398 and 74F399 are high-speed quad 2-port registers. They select four bits of data from either of two sources (Ports) under control of a common Select input (S). The selected data is transferred to a 4-bit output register synchronous with the LOW-to-HIGH transition of the Clock input (CP). The 4-bit D-type output register is fully edge-triggered. The Data inputs (I_{0x}, I_{1x}) and Select input (S) must be stable only a setup time prior to and hold time after the LOW-to-HIGH transition of the Clock input for predictable operation. The 74F398 has both Q and $\overline{Q}$ outputs.

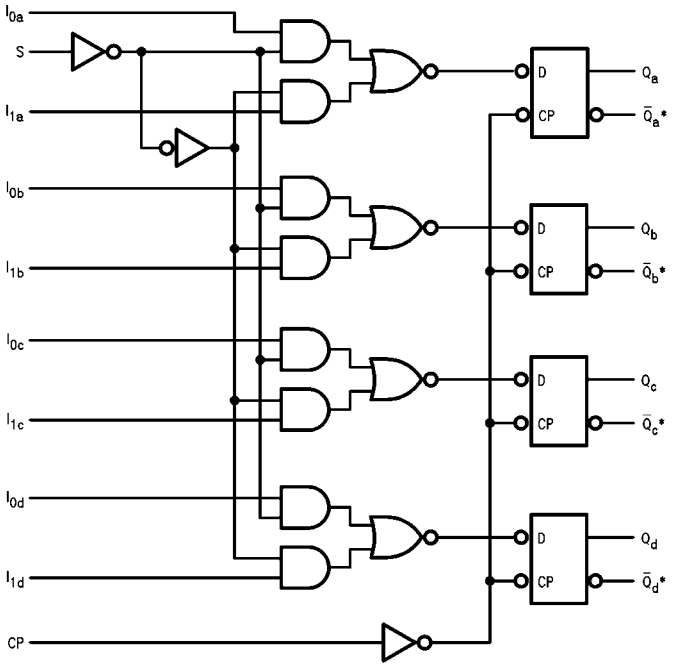
Function Table

Inputs			Outputs	
S	**I_0**	**I_1**	**Q**	**$\overline{Q}$ (Note 1)**
l	l	X	L	H
l	h	X	H	L
h	X	l	L	H
h	X	h	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH clock transition
l = LOW Voltage Level one setup time prior to the LOW-to-HIGH clock transition
X = Immaterial

Note 1: 74F398 only

Logic Diagram



*F398 Only

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL}(mA)
ESD Last Passing Voltage	
(Min)—74F399	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current (74F398)			25	38	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F398)			25	38	mA	Max	V_O = LOW
I_{CCH}	Power Supply Current (74F399)			22	34	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F399)			22	34	mA	Max	V_O = LOW

AC Electrical Characteristics

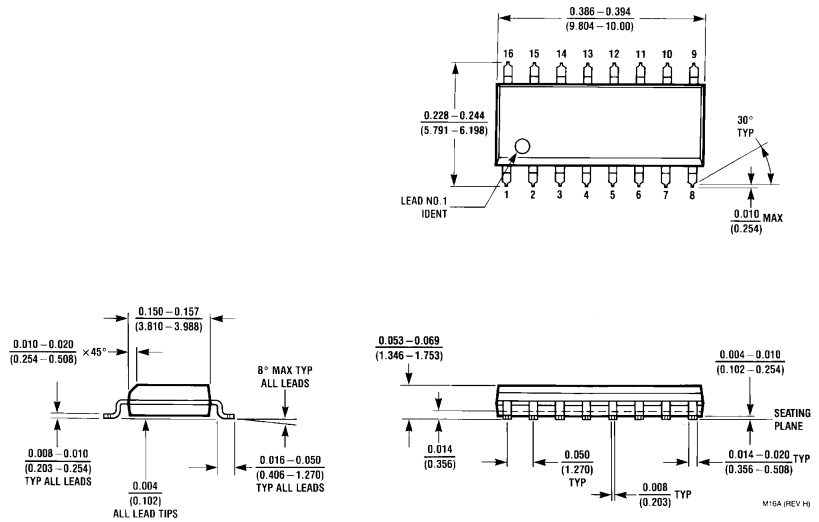
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Input Clock Frequency	100	140		100		MHz
t_{PLH}	Propagation Delay	3.0 (Note 4)	5.7	7.5	3.0	8.5	ns
t_{PHL}	CP to Q or $\overline{Q}$	3.0	6.8	9.0	3.0	10.0	

Note 4: 74F398 3.3 ns

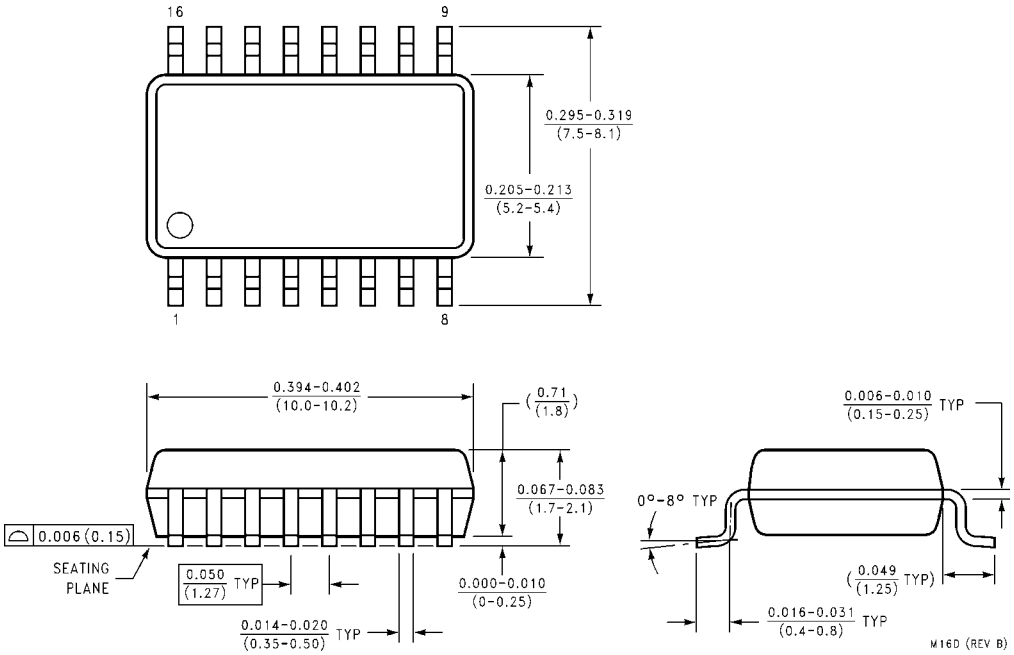
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.0		ns
$t_S(L)$	I_n to CP	3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.0		
$t_H(L)$	I_n to CP	1.0		1.0		
$t_S(H)$	Setup Time, HIGH or LOW	7.5		8.5		ns
$t_S(L)$	S to CP (F398)	7.5		8.5		
$t_S(H)$	Setup Time, HIGH or LOW	7.5		8.5		
$t_S(L)$	S to CP (F399)	7.5		8.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	S to CP	0		0		
$t_W(H)$	CP Pulse Width	4.0		4.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted

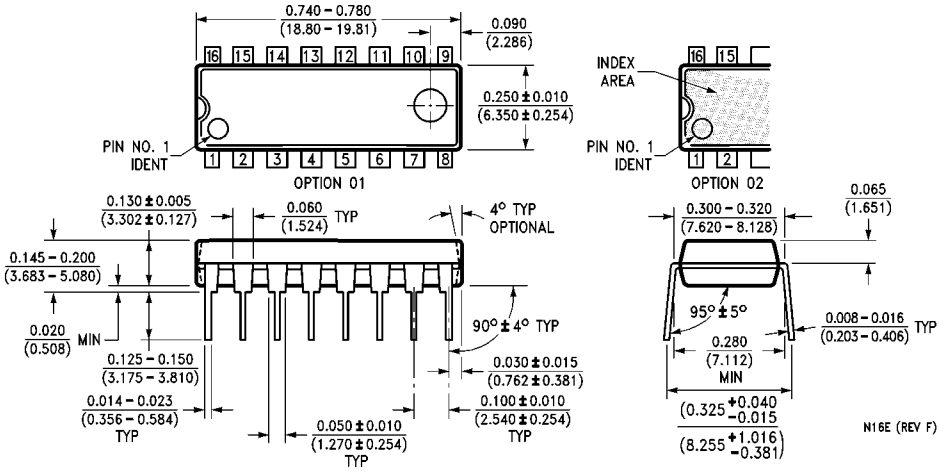


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow Body
Package Number M16A

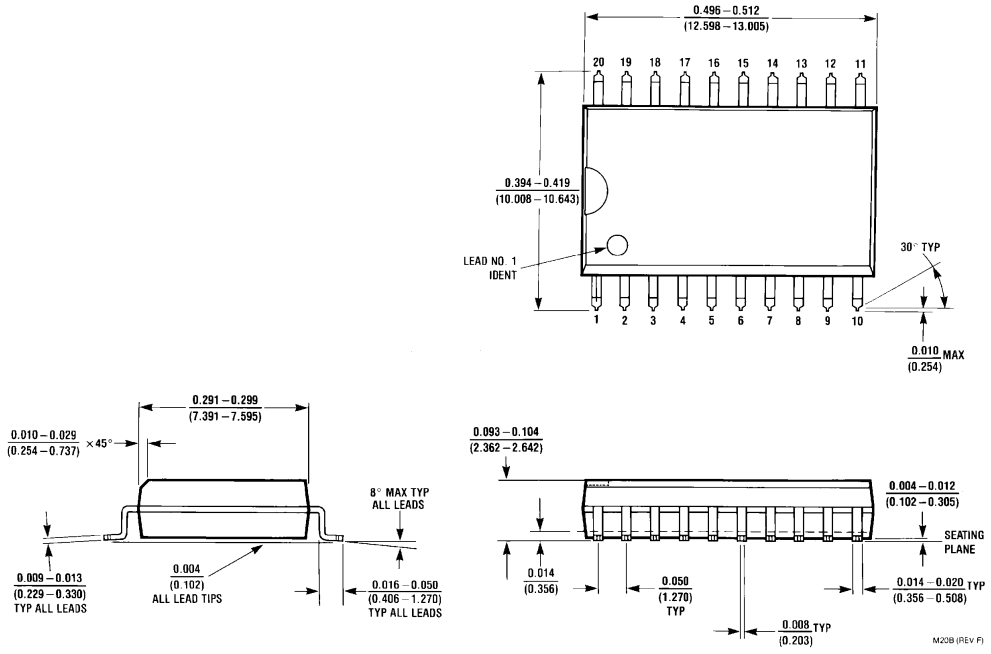


16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

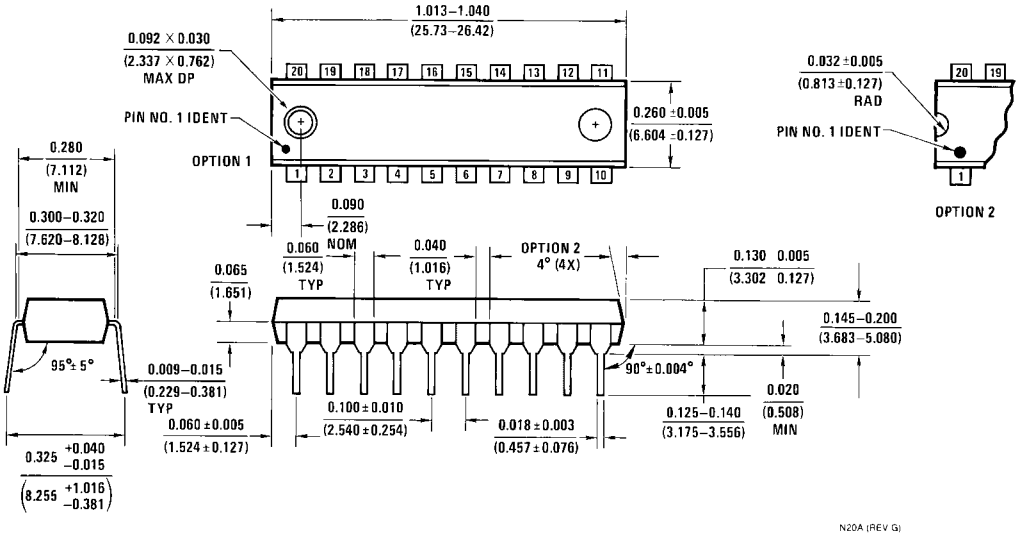


16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F401
CRC Generator/Checker

General Description

The 74F401 Cycle Redundancy Check (CRC) Generator/Checker provides an advanced tool for implementing the most widely used error detection scheme in serial digital data handling systems. A 3-bit control input selects one-of-eight generator polynomials. The list of polynomials includes CRC-16 and CRC-CCITT as well as their reciprocals (reverse polynomials). Automatic right justification is incorporated for polynomials of degree less than 16. Separate clear and preset inputs are provided for floppy disk and other applications. The Error output indicates whether or not a transmission error has occurred. Another control input inhibits feedback during check word transmission. The 74F401 is fully compatible with all TTL families.

Features

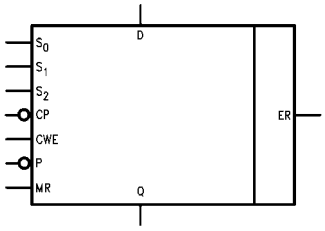
- Eight selectable polynomials
- Error indicator
- Separate preset and clear controls
- Automatic right justification
- Fully compatible with all TTL logic families
- 14-pin package
- 9401 equivalent
- Typical applications:
  - Floppy and other disk storage systems
  - Digital cassette and cartridge systems
  - Data communication systems

Ordering Code:

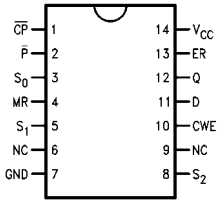
Order Number	Package Number	Package Description
74F401SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F401PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0–S_2	Polynomial Select Inputs	1.0/1.0	20 µA/–0.6 mA
D	Data Input	1.0/1.0	20 µA/–0.6 mA
$\overline{CP}$	Clock Input (Operates on HIGH-to-LOW Transition)	1.0/1.0	20 µA/–0.6 mA
CWE	Check Word Enable Input	1.0/1.0	20 µA/–0.6 mA
$\overline{P}$	Preset (Active LOW) Input	1.0/1.0	20 µA/–0.6 mA
MR	Master Reset (Active HIGH) Input	1.0/1.0	20 µA/–0.6 mA
Q	Data Output	50/33.3	–1 mA/20 mA
ER	Error Output	50/33.3	–1 mA/20 mA

Functional Description

The 74F401 is a 16-bit programmable device which operates on serial data streams and provides a means of detecting transmission errors. Cyclic encoding and decoding schemes for error detection are based on polynomial manipulation in modulo arithmetic. For encoding, the data stream (message polynomial) is divided by a selected polynomial. This division results in a remainder which is appended to the message as check bits. For error checking, the bit stream containing both data and check bits is divided by the same selected polynomial. If there are no detectable errors, this division results in a zero remainder. Although it is possible to choose many generating polynomials of a given degree, standards exist that specify a small number of useful polynomials. The 74F401 implements the polynomials listed in Table 1 by applying the appropriate logic levels to the select pins S_0, S_1 and S_2.

The 74F401 consists of a 16-bit register, a Read Only Memory (ROM) and associated control circuitry as shown in the block diagram. The polynomial control code presented at inputs S_0, S_1 and S_2 is decoded by the ROM, selecting the desired polynomial by establishing shift mode operation on the register with Exclusive OR gates at appropriate inputs. To generate the check bits, the data stream is entered via the Data inputs (D), using the HIGH-to-LOW transition of the Clock input ($\overline{CP}$). This data is gated with the most significant output (Q) of the register, and controls the Exclusive OR gates Figure 1. The Check Word Enable (CWE) must be held HIGH while the data is being entered. After the last data bit is entered, the CWE is brought LOW and the check bits are shifted out of the register and appended to the data bits using external gating Figure 2.

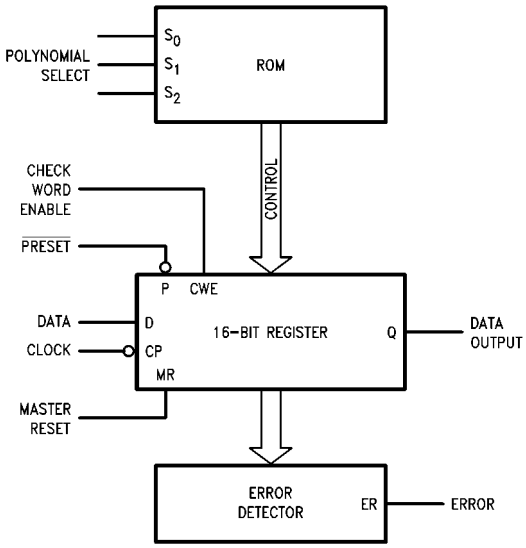
To check an incoming message for errors, both the data and check bits are entered through the D input with the CWE input held HIGH. The 74F401 is not in the data path, but only monitors the message. The Error Output becomes valid after the last check bit has been entered into the 74F401 by a HIGH-to-LOW transition of $\overline{CP}$. If no detectable errors have occurred during the data transmission, the resultant internal register bits are all LOW and the Error Output (ER) is LOW. If a detectable error has occurred, ER is HIGH.

A HIGH on the Master Reset input (MR) asynchronously clears the register. A LOW on the Preset input ($\overline{P}$) asynchronously sets the entire register if the control code inputs specify a 16-bit polynomial; in the case of 12- or 8-bit check polynomials only the most significant 12 or 8 register bits are set and the remaining bits are cleared.

TABLE 1.

Select Code S_2	Select Code S_1	Select Code S_0	Polynomial	Remarks
L	L	L	$X^{16} + X^{15} + X^2 + 1$	CRC-16
L	L	H	$X^{16} + X^{14} + X + 1$	CRC-16 REVERSE
L	H	L	$X^{16} + X^{15} + X^{13} + X^7 + X^4 + X^2 + X^1 + 1$	
L	H	H	$X^{12} + X^{11} + X^3 + X^2 + X + 1$	CRC-12
H	L	L	$X^8 + X^7 + X^5 + X^4 + X + 1$	
H	L	H	$X^8 + 1$	LRC-8
H	H	L	$X^{16} + X^{12} + X^5 + 1$	CRC-CCITT
H	H	H	$X^{16} + X^{11} + X^4 + 1$	CRC-CCITT REVERSE

Block Diagram



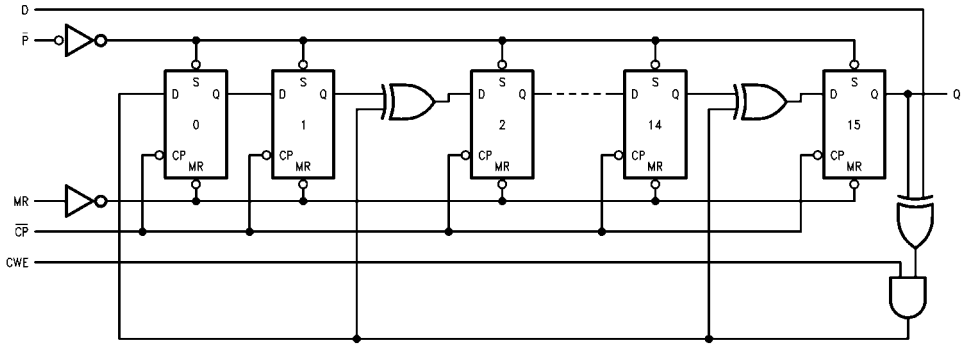


FIGURE 1. Equivalent Circuit for $X^{16} + X^{15} + X^2 + 1$

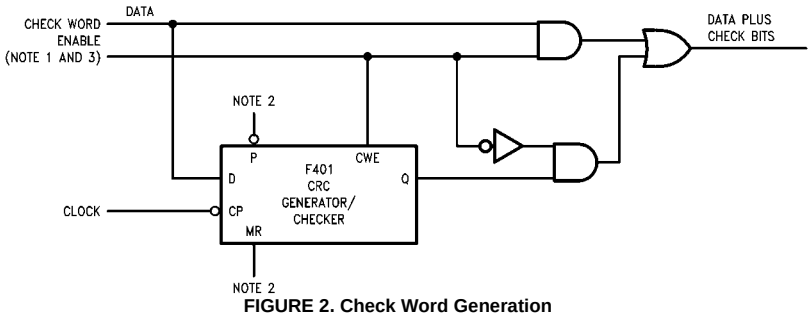


FIGURE 2. Check Word Generation

Note 1: Check word Enable is HIGH while data is being clocked, LOW while transmission of check bits.

Note 2: 74F401 must be reset or preset before each computation.

Note 3: CRC check bits are generated and appended to data bits.

Absolute Maximum Ratings(Note 4)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 5)	−0.5V to +7.0V
Input Current (Note 5)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 4: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 5: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			70	105	mA	Max	V_O = HIGH

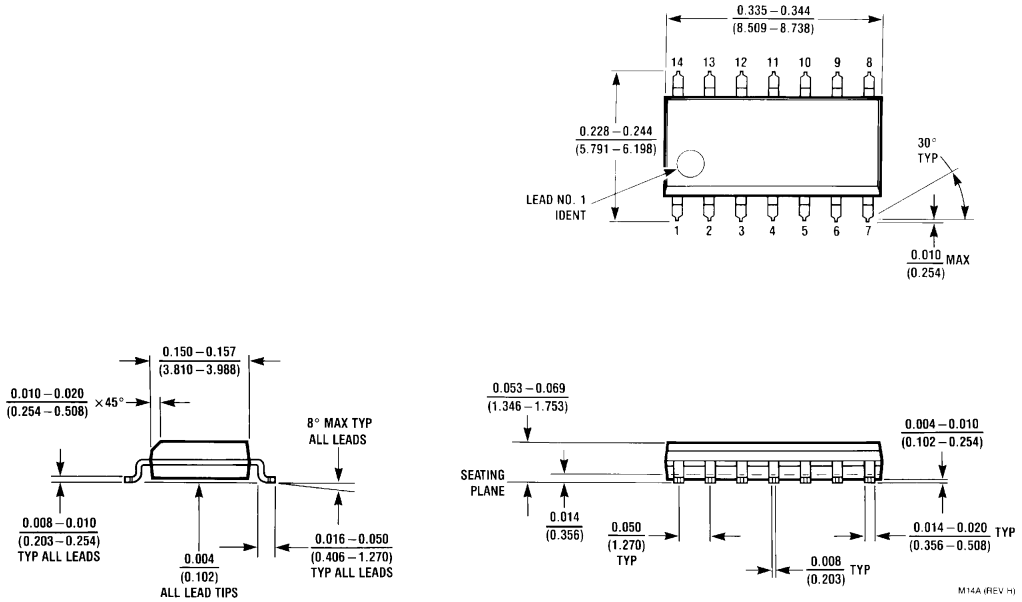
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100			85		MHz
t_{PLH}	Propagation Delay	4.5		11.5	4.5	13.5	ns
t_{PHL}	$\overline{CP}$ to Q	4.0		10.0	4.0	11.0	
t_{PHL}	Propagation Delay MR to Q	3.0		7.5	3.0	8.0	ns
t_{PLH}	Propagation Delay $\overline{P}$ to Q	3.0		8.5	3.0	9.5	ns
t_{PHL}	Propagation Delay MR to ER	3.5		11.0	3.5	12.0	ns
t_{PLH}	Propagation Delay $\overline{P}$ to ER	3.0		8.5	3.0	10.0	ns
t_{PLH}	Propagation Delay	5.0		13.0	5.0	14.5	ns
t_{PHL}	$\overline{CP}$ to ER	4.5		11.5	4.5	12.5	

AC Operating Requirements

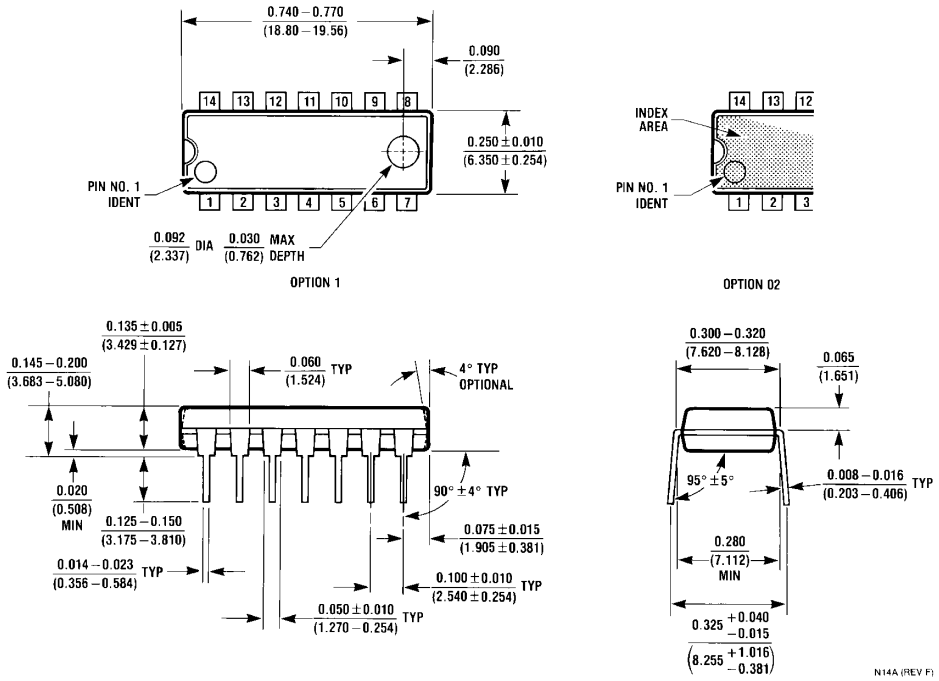
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Set-up Time, HIGH or LOW	5.0		5.5		
$t_S(L)$	D to $\overline{CP}$	5.0		5.5		
$t_S(H)$	Set-up Time, HIGH or LOW	4.0		4.5		ns
$t_S(L)$	CWE to $\overline{CP}$	4.0		4.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		
$t_H(L)$	D and CWE to $\overline{CP}$	2.0		2.0		
$t_W(L)$	$\overline{P}$ Pulse Width, LOW	7.0		8.0		ns
$t_W(H)$	Clock Pulse Width,	5.0		6.0		ns
$t_W(L)$	HIGH or LOW	5.0		6.0		
$t_W(H)$	MR Pulse Width, HIGH	5.0		5.5		ns
t_{REC}	Recovery Time MR to $\overline{CP}$	4.0		4.5		ns
t_{REC}	Recovery Time $\overline{P}$ to $\overline{CP}$	2.0		2.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F402
Serial Data Polynomial Generator/Checker

General Description

The 74F402 expandable Serial Data Polynomial generator/checker is an expandable version of the 74F401. It provides an advanced tool for the implementation of the most widely used error detection scheme in serial digital handling systems. A 4-bit control input selects one-of-six generator polynomials. The list of polynomials includes CRC-16, CRC-CCITT and Ethernet®, as well as three other standard polynomials (56^{th} order, 48^{th} order, 32^{nd} order). Individual clear and preset inputs are provided for floppy disk and other applications. The Error output indicates whether or not a transmission error has occurred. The CWG Control input inhibits feedback during check word transmission. The 74F402 is compatible with FAST® devices and with all TTL families.

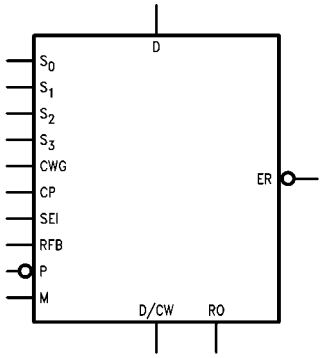
Features

- Guaranteed 30 MHz data rate
- Six selectable polynomials
- Other polynomials available
- Separate preset and clear controls
- Expandable
- Automatic right justification
- Error output open collector
- Typical applications: Floppy and other disk storage systems Digital cassette and cartridge systems Data communication systems

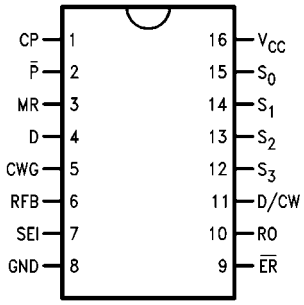
Ordering Code:

Order Number	Package Number	Package Description
74F402PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Logic Symbol



Connection Diagram



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Ethernet® is a registered trademark of Xerox Corporation.

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0–S_3	Polynomial Select Inputs	1.0/0.67	20 µA/–0.4 mA
CWG	Check Word Generate Input	1.0/0.67	20 µA/–0.4 mA
D/CW	Serial Data/Check Word	285(100)/13.3(6.7)	–5.7 mA(–2 mA)/8 mA (4 mA)
D	Data Input	1.0/0.67	20 µA/–0.4 mA
$\overline{ER}$	Error Output	(Note 1) /26.7(13.3)	(Note 1) /16 mA (8 mA)
RO	Register Output	285(100)/13.3(6.7)	–5.7 mA(–2 mA)/8 mA (4 mA)
CP	Clock Pulse	1.0/0.67	20 µA/–0.4 mA
SEI	Serial Expansion Input	1.0/0.67	20 µA/–0.4 mA
RFB	Register Feedback	1.0/0.67	20 µA/–0.4 mA
MR	Master Reset	1.0/0.67	20 µA/–0.4 mA
$\overline{P}$	Preset	1.0/0.67	20 µA/–0.4 mA

Note 1: Open Collector

Functional Description

The 74F402 Serial Data Polynomial Generator/Checker is an expandable 16-bit programmable device which operates on serial data streams and provides a means of detecting transmission errors. Cyclic encoding and decoding schemes for error detection are based on polynomial manipulation in modulo arithmetic. For encoding, the data stream (message polynomial) is divided by a selected polynomial. This division results in a remainder (or residue) which is appended to the message as check bits. For error checking, the bit stream containing both data and check bits is divided by the same selected polynomial. If there are no detectable errors, this division results in a zero remainder. Although it is possible to choose many generating polynomials of a given degree, standards exist that specify a small number of useful polynomials. The 74F402 implements the polynomials listed in Table 1 by applying the appropriate logic levels to the select pins S_0, S_1, S_2 and S_3.

The 74F402 consists of a 16-bit register, a Read Only Memory (ROM) and associated control circuitry as shown in the Block Diagram. The polynomial control code presented at inputs S_0, S_1, S_2 and S_3 is decoded by the ROM, selecting the desired polynomial or part of a polynomial by establishing shift mode operation on the register with Exclusive OR (XOR) gates at appropriate inputs. To generate the check bits, the data stream is entered via the Data Inputs (D), using the LOW-to-HIGH transition of the Clock Input (CP). This data is gated with the most significant Register Output (RO) via the Register Feedback Input (RFB), and controls the XOR gates. The Check Word Generate (CWG) must be held HIGH while the data is being entered. After the last data bit is entered, the CWG is brought LOW and the check bits are shifted out of the register(s) and appended to the data bits (no external gating is needed).

To check an incoming message for errors, both the data and check bits are entered through the D Input with the CWG Input held HIGH. The Error Output becomes valid after the last check bit has been entered into the 'F402 by a LOW-to-HIGH transition of CP, with the exception of the Ethernet polynomial (see Applications paragraph). If no detectable errors have occurred during the data transmission, the resultant internal register bits are all LOW and the Error Output ($\overline{ER}$) is HIGH. If a detectable error has occurred, $\overline{ER}$ is LOW. $\overline{ER}$ remains valid until the next LOW-to-HIGH transition of CP or until the device has been preset or reset.

A HIGH on the Master Reset Input (MR) asynchronously clears the entire register. A LOW on the Preset Input ($\overline{P}$) asynchronously sets the entire register with the exception of:

1. The Ethernet residue selection, in which the registers containing the non-zero residue are cleared;
2. The 56th order polynomial, in which the 8 least significant register bits of the least significant device are cleared; and,
3. Register S = 0, in which all bits are cleared.

TABLE 1.

Hex	Select Code S_3	S_2	S_1	S_0	Polynomial	Remarks
0	L	L	L	L	0	S = 0
C	H	H	L	L	$X^{32}+X^{26}+X^{23}+X^{22}+X^{16}+$	Ethernet
D	H	H	L	H	$X^{12}+X^{11}+X^{10}+X^{8}+X^{7}+X^{5}+X^{4}+X^{2}+X+1$	Polynomial
E	H	H	H	L	$X^{32}+X^{31}+X^{27}+X^{26}+X^{25}+X^{19}+X^{16}+$	Ethernet
F	H	H	H	H	$X^{15}+X^{13}+X^{12}+X^{11}+X^{9}+X^{7}+X^{6}+X^{5}+X^{4}+X^{2}+X+1$	Residue
7	L	H	H	H	$X^{16}+X^{15}+X^{2}+1$	CRC-16
B	H	L	H	H	$X^{16}+X^{12}+X^{5}+1$	CRC-CCITT
3	L	L	H	H	$X^{56}+X^{55}+X^{49}+X^{45}+X^{41}+$	
2	L	L	H	L	$X^{39}+X^{38}+X^{37}+X^{36}+X^{31}+$	56th
4	L	H	L	L	$X^{22}+X^{19}+X^{17}+X^{16}+X^{15}+X^{14}+X^{12}+X^{11}+X^{9}+$	Order
8	H	L	L	L	$X^{5}+X+1$	
5	L	H	L	H	$X^{48}+X^{36}+X^{35+}$	
9	H	L	L	H	$X^{23}+X^{21}+$	48th
1	L	L	L	H	$X^{15}+X^{13}+X^{8}+X^{2}+1$	Order
6	L	H	H	L	$X^{32}+X^{23}+X^{21}+$	32nd
A	H	L	H	L	$X^{11}+X^{2}+1$	Order

Block Diagram

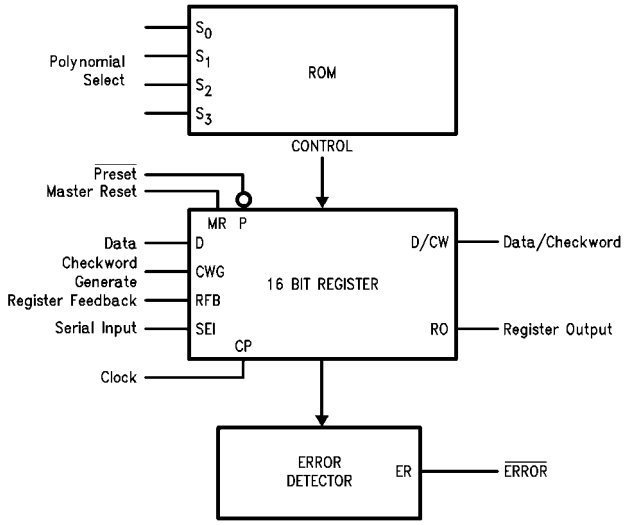


TABLE 2.

Select Code	P_3	P_2	P_1	P_0	C_2	C_1	C_0	Polynomial
0	0	0	0	0	1	0	0	S = 0
C	1	1	1	1	1	0	1	Ethernet
D	1	1	1	1	1	0	1	Polynomial
E	0	0	0	0	0	0	0	Ethernet
F	0	0	0	0	0	1	0	Residue
7	1	1	1	1	1	0	0	CRC-16
B	1	1	1	1	1	0	0	CRC-CCITT
3	1	1	1	1	1	0	0	
2	1	1	1	1	1	0	0	56th
4	1	1	1	1	1	0	0	Order
8	0	0	1	1	1	0	0	
5	1	1	1	1	1	0	0	48th
9	1	1	1	1	1	0	0	Order
1	1	1	1	1	1	0	0	
6	1	1	1	1	1	0	0	32nd
A	1	1	1	1	1	0	0	Order

Applications

In addition to polynomial selection there are four other capabilities provided for in the 74F402 ROM. The first is set or clear selectability. The sixteen internal registers have the capability to be either set or cleared when $\overline{P}$ is brought LOW. This set or clear capability is done in four groups of 4 (see Table 2, P_0–P_3). The second ROM capability (C_0) is in determining the polarity of the check word. As is the case with the Ethernet polynomial the check word can be inverted when it is appended to the data stream or as is the case with the other polynomials, the residue is appended with no inversion. Thirdly, the ROM contains a bit (C_1) which is used to select the RFB input instead of the SEI input to be fed into the LSB. This is used when the polynomial selected is actually a residue (least significant) stored in the ROM which indicates whether the selected location is a polynomial or a residue. If the latter, then it inhibits the RFB input.

As mentioned previously, upon a successful data transmission, the CRC register has a zero residue. There is an exception to this, however, with respect to the Ethernet polynomial. This polynomial, upon a successful data transmission, has a non-zero residue in the CRC register (C7 04 DD 7B)$_{16}$. In order to provide a no-error indication, two ROM locations have been preloaded with the residue so that by selecting these locations and clocking the device one additional time, after the last check bit has been entered, will result in zeroing the CRC register. In this manner a no-error indication is achieved.

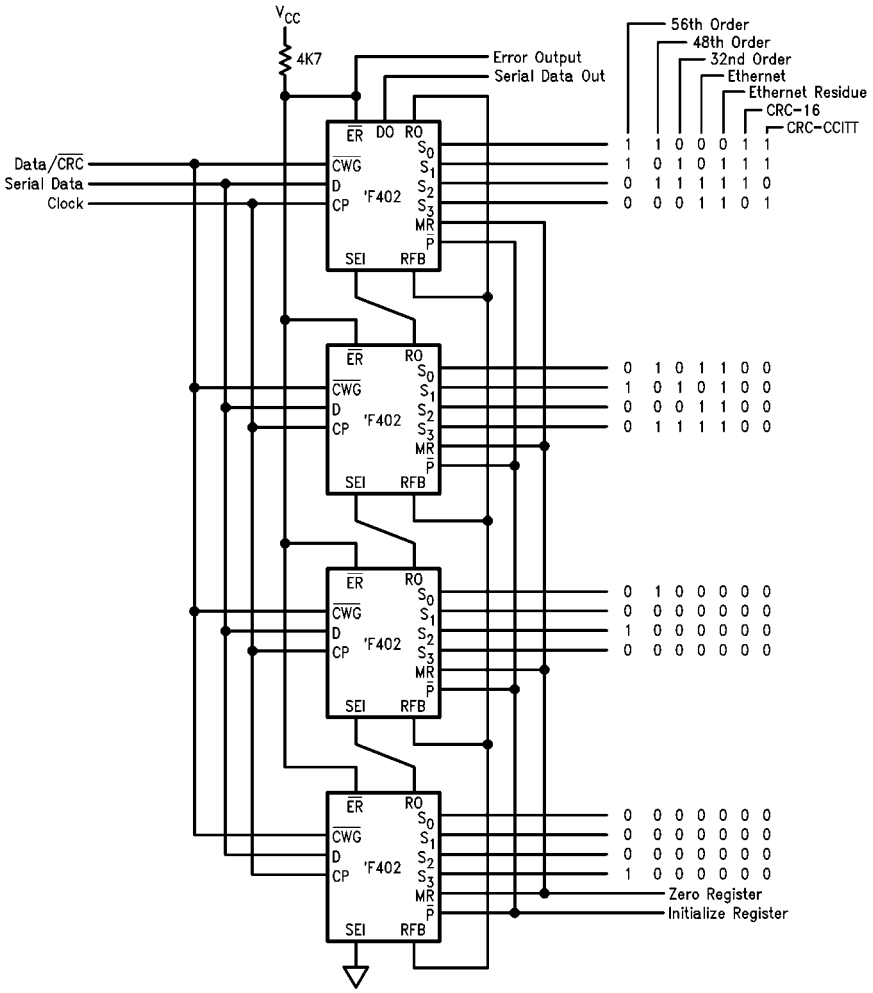
With the present mix of polynomials, the largest is 56th order requiring four devices while the smallest is 16th order requiring just one device. In order to accommodate multiplexing between high order polynomials (X 16th order) and lower order polynomials, a location of all zeros is provided. This allows the user to choose a lower order polynomial even if the system is configured for a higher order one.

The 74F402 expandable CRC generator checker contains 6 popular CRC polynomials, 2-16th Order, 2-32nd Order, 1-48th Order and 1-56th Order. The application diagram shows the 74F402 connected for a 56th Order polynomial. Also shown are the input patterns for other polynomials. When the 74F402 is used with a gated clock, disabling the clock in a HIGH state will ensure no erroneous clocking occurs when the clock is re-enabled. Preset and Master Reset are asynchronous inputs presetting the register to S or clearing to 1s respectively (note Ethernet residue and 56th Order select code 8, LSB, are exceptions to this).

To generate a CRC, the pattern for the selected polynomial is applied to the S inputs, the register is preset or cleared as required, clock is enabled, CWG is set HIGH, data is applied to D input, output data is on D/CW. When the last data bit has been entered, CWG is set LOW and the register is clocked for n bits (where n is the order of the polynomial). The clock may now be stopped if desired (holding CWG LOW and clocking the register will output zeros from D/CW after the residue has been shifted out).

To check a CRC, the pattern for the selected polynomial is applied to the S inputs, the register is preset or cleared as required, clock is enabled, CWG is set HIGH, the data stream including the CRC is applied to D input. When the last bit of the CRC has been entered, the $\overline{ER}$ output is checked: HIGH = error free data, LOW = corrupt data. The clock may now be stopped if desired.

To implement polynomials of lower order than 56th, select the number of packages required for the order of polynomial and apply the pattern for the selected polynomial to the S inputs (0000 on S inputs disables the package from the feedback chain).


V_{CC}
4K7
Error Output
Serial Data Out
56th Order
48th Order
32nd Order
Ethernet
Ethernet Residue
CRC-16
CRC-CCITT
Data/CRC
Serial Data
Clock
ER
DO
RO
CWG
D
CP
'F402
S_0
S_1
S_2
S_3
MR
P
SEI
RFB
1 1 0 0 0 1 1
1 0 1 0 1 1 1
0 1 1 1 1 1 0
0 0 0 1 1 0 1
0 1 0 1 1 0 0
1 0 1 0 1 0 0
0 0 0 1 1 0 0
0 1 1 1 1 0 0
0 1 0 0 0 0 0
0 0 0 0 0 0 0
1 0 0 0 0 0 0
0 0 0 0 0 0 0
0 0 0 0 0 0 0
0 0 0 0 0 0 0
0 0 0 0 0 0 0
1 0 0 0 0 0 0
Zero Register
Initialize Register

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −5.7 mA (RO, D/CW)
		5% V_{CC}	2.7					I_{OH} = −5.7 mA (RO, D/CW)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5			I_{OL} = 16 mA ($\overline{ER}$)
		10% V_{CC}			0.5			I_{OL} = 8 mA (D/CW, RO)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.4	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−20		−130	mA	Max	V_{OUT} = 0V (D/CW, RO)
I_{OHC}	Open Collector, Output OFF Leakage Test				250	µA	Min	V_{OUT} = V_{CC} ($\overline{ER}$)
I_{CC}	Power Supply Current			110	165	mA	Max	

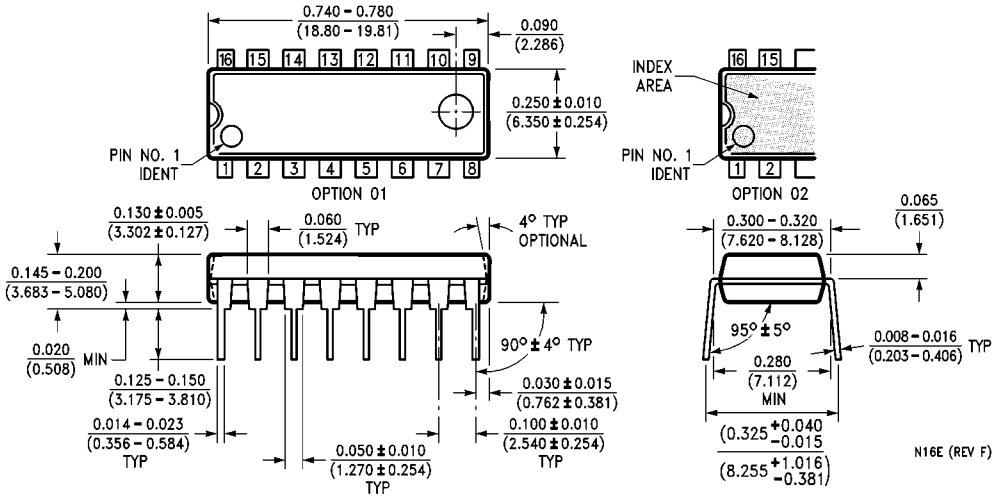
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	30	45		30		30		MHz
t_{PLH}	Propagation Delay	8.5	15.0	19.0	7.5	26.5	7.5	21.0	ns
t_{PHL}	CP to D/CW	10.5	18.0	23.0	9.5	26.5	9.5	25.0	
t_{PLH}	Propagation Delay	8.0	13.5	17.0	7.0	26.0	7.0	19.0	ns
t_{PHL}	CP to RO	8.0	14.0	18.0	7.0	22.5	7.0	20.0	
t_{PLH}	Propagation Delay	15.5	26.0	33.0	14.0	38.5	14.0	35.0	ns
t_{PHL}	CP to $\overline{ER}$	8.5	14.5	18.5	7.5	23.5	7.5	20.5	
t_{PLH}	Propagation Delay	11.0	18.5	23.5	10.0	31.0	10.0	25.5	ns
t_{PHL}	$\overline{P}$ to D/CW	11.5	19.5	24.5	10.5	32.0	10.5	26.5	
t_{PLH}	Propagation Delay $\overline{P}$ to RO	9.5	16.0	20.5	8.5	31.5	8.5	22.5	ns
t_{PLH}	Propagation Delay $\overline{P}$ to $\overline{ER}$	10.0	17.0	21.5	9.0	26.0	9.0	23.5	ns
t_{PLH}	Propagation Delay	10.5	18.0	23.0	9.5	29.0	9.5	25.5	ns
t_{PHL}	MR to D/CW	11.0	19.0	24.0	10.0	28.5	10.0	26.0	
t_{PHL}	Propagation Delay MR to RO	9.0	15.5	19.5	8.0	23.5	8.0	21.5	ns
t_{PLH}	Propagation Delay MR to $\overline{ER}$	16.5	28.0	35.5	14.5	39.0	14.5	37.5	ns
t_{PLH}	Propagation Delay	6.0	10.5	13.5	5.0	19.5	5.0	15.0	ns
t_{PHL}	D to D/CW	7.5	12.0	16.0	6.5	20.0	6.5	18.0	
t_{PLH}	Propagation Delay	6.5	11.0	14.0	5.5	21.5	5.5	15.5	ns
t_{PHL}	CWG to D/CW	7.0	12.0	15.5	6.0	21.5	6.0	17.5	
t_{PLH}	Propagation Delay	11.5	19.5	24.5	9.0	29.0	10.5	26.5	ns
t_{PHL}	S_n to D/CW	9.5	16.0	20.0	8.5	25.0	8.5	22.0	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.5		6.0		5.0		ns
$t_S(L)$	SEI to CP	4.5		6.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		1.0		0		
$t_H(L)$	SEI to CP	0		1.0		0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		14.0		12.5		ns
$t_S(L)$	RFB to CP	11.0		14.0		12.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	RFB to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	13.5		16.0		15.0		ns
$t_S(L)$	S_1 to CP	13.0		15.5		14.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	S_1 to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	9.0		11.5		10.0		ns
$t_S(L)$	D to CP	9.0		11.5		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	D to CP	0		0		0		
$t_S(H)$	Setup Time, HIGH or LOW	7.0		9.0		8.0		ns
$t_S(L)$	CWG to CP	5.5		8.0		6.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		0		
$t_H(L)$	CWG to CP	0		0		0		
$t_W(H)$	Clock Pulse Width	4.0		7.0		4.5		ns
$t_W(L)$	HIGH or LOW	4.0		5.0		4.5		
$t_W(H)$	MR Pulse Width, HIGH	4.0		7.0		4.5		ns
$t_W(L)$	$\overline{P}$ Pulse Width, LOW	4.0		5.0		4.5		ns
t_{REC}	Recovery Time MR to CP	3.0		4.0		3.5		ns
t_{REC}	Recovery Time $\overline{P}$ to CP	5.0		6.5		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

January 1989
Revised May 1999

74F403A
First-In First-Out (FIFO) Buffer Memory

General Description

The 74F403A is an expandable fall-through type high-speed First-In First-Out (FIFO) Buffer Memory optimized for high-speed disk or tape controllers and communication buffer applications. It is organized as 16-words by 4-bits and may be expanded to any number of words or any number of bits in multiples of four. Data may be entered or extracted asynchronously in serial or parallel, allowing economical implementation of buffer memories.

The 74F403A has 3-STATE outputs which provide added versatility and is fully compatible with all TTL families.

Features

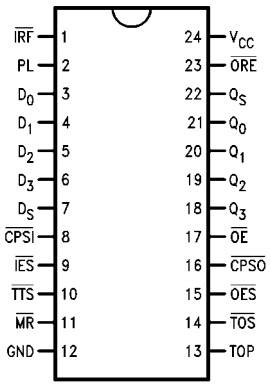
- Serial or parallel input
- Serial or parallel output
- Expandable without external logic
- 3-STATE outputs
- Fully compatible with all TTL families
- Slim 24-pin package
- 9403A replacement
- Guaranteed 4000V minimum ESD protection

Ordering Code:

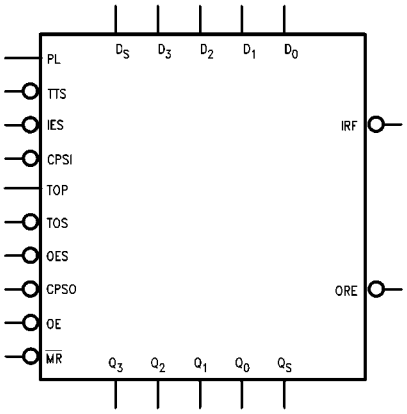
Order Number	Package Number	Package Description
74F403ASPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol

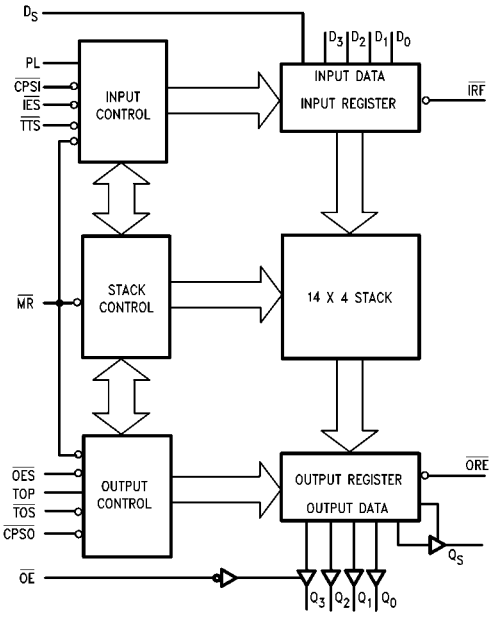


Unit Loading/Fan Out:

See Section 2 for U.L. definitions

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$D_0 - D_3$	Parallel Data Inputs	1.0/0.667	20 µA/400 µA
D_S	Serial Data Input	1.0/0.667	20 µA/400 µA
PL	Parallel Load Input	1.0/0.667	20 µA/400 µA
$\overline{CPSI}$	Serial Input Clock	1.0/0.667	20 µA/400 µA
$\overline{IES}$	Serial Input Enable	1.0/0.667	20 µA/400 µA
$\overline{TTS}$	Transfer to Stack Input	1.0/0.667	20 µA/400 µA
$\overline{OES}$	Serial Output Enable	1.0/0.667	20 µA/400 µA
$\overline{TOS}$	Transfer Out Serial	1.0/0.667	20 µA/400 µA
TOP	Transfer Out Parallel	1.0/0.667	20 µA/400 µA
$\overline{MR}$	Master Reset	1.0/0.667	20 µA/400 µA
$\overline{OE}$	Output Enable	1.0/0.667	20 µA/400 µA
$\overline{CPSO}$	Serial Output Clock	1.0/0.667	20 µA/400 µA
$Q_0 - Q_3$	Parallel Data Outputs	285/26.7	5.7 mA/16 mA
Q_S	Serial Data Output	285/26.7	5.7 mA/16 mA
$\overline{IRF}$	Input Register Full	20/13.3	−400 µA/8 mA
$\overline{ORE}$	Output Register Empty	20/13.3	−400 µA/8 mA

Block Diagram



Functional Description

As shown in the Block Diagram the 74F403A consists of three sections:

1. An Input register with parallel and serial data inputs as well as control inputs and outputs for input handshaking and expansion.
2. A 4-bit wide, 14-word deep fall-through stack with self-contained control logic.
3. An Output Register with parallel and serial data outputs as well as control inputs and outputs for output handshaking and expansion.

Since these three sections operate asynchronously and almost independently, they will be described separately below.

INPUT REGISTER (DATA ENTRY)

The Input Register can receive data in either bit-serial or in 4-bit parallel form. It stores this data until it is sent to the fall-through stack and generates the necessary status and control signals.

Figure 1 is a conceptual logic diagram of the input section. As described later, this 5-bit register is initialized by setting the F_3 flip-flop and resetting the other flip-flops. The $\overline{Q}$ output of the last flip-flop (FC) is brought out as the "Input Register Full" output ($\overline{IRF}$). After initialization this output is HIGH.

Parallel Entry— A HIGH on the PL input loads the D_0-D_3 inputs into the F_0-F_3 flip-flops and sets the FC flip-flop. This forces the $\overline{IRF}$ output LOW indicating that the input register is full. During parallel entry, the $\overline{CPSI}$ input must be LOW. If parallel expansion is not being implemented, $\overline{IES}$ must be LOW to establish row mastership (see Expansion section).

Serial Entry— Data on the D_S input is serially entered into the F_3, F_2, F_1, F_0, FC shift register on each HIGH-to-LOW transition of the $\overline{CPSI}$ clock input, provided $\overline{IES}$ and PL are LOW.

After the fourth clock transition, the four data bits are located in the four flip-flops, F_0-F_3. The FC flip-flop is set, forcing the $\overline{IRF}$ output LOW and internally inhibiting $\overline{CPSI}$ clock pulses from affecting the register, Figure 2 illustrates the final positions in a 74F403A resulting from a 64-bit serial bit train. B_0 is the first bit, B_{63} the last bit.

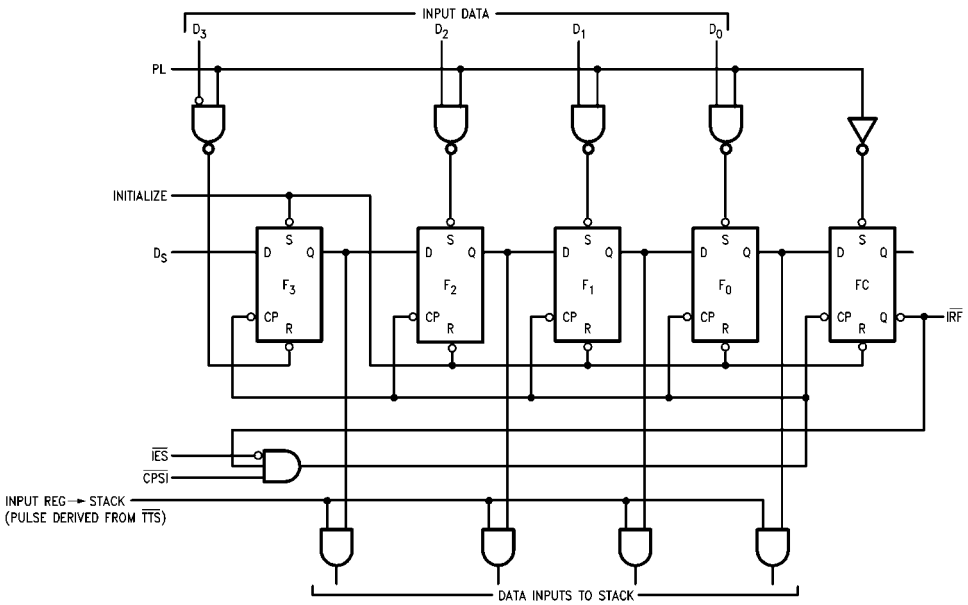


FIGURE 1. Conceptual Input Section

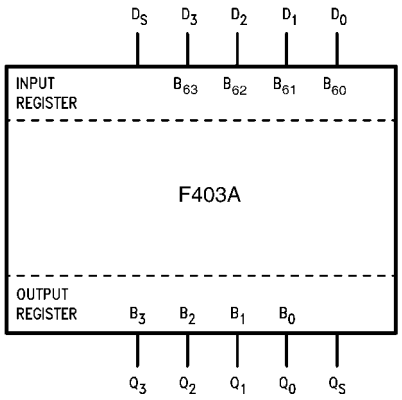


FIGURE 2. Final Positions in a 74F403A Resulting from a 64-Bit Serial Train

Transfer to the Stack— The outputs of Flip-Flops F_0-F_3 feed the stack. A LOW level on the $\overline{TTS}$ input initiates a "fall-through" action. If the top location of the stack is empty, data is loaded into the stack and the input register is re-initialized. Note that this initialization is postponed until PL is LOW again. Thus, automatic FIFO action is achieved by connecting the $\overline{IRF}$ output to the $\overline{TTS}$ input.

An RS Flip-Flop (the Request Initialization Flip-Flop shown in Figure 10) in the control section records the fact that data has been transferred to the stack. This prevents multiple entry of the same word into the stack despite the fact the $\overline{IRF}$ and $\overline{TTS}$ may still be LOW. The Request Initialization Flip-Flop is not cleared until PL goes LOW. Once in the stack, data falls through the stack automatically, pausing only when it is necessary to wait for an empty next location. In the 74F403A as in most modern FIFO designs, the $\overline{MR}$ input only initializes the stack control section and does not clear the data.

OUTPUT REGISTER (DATA EXTRACTION)

The Output Register receives 4-bit data words from the bottom stack location, stores it and outputs data on a 3-STATE 4-bit parallel data bus or on a 3-STATE serial data bus. The output section generates and receives the necessary status and control signals. Figure 3 is a conceptual logic diagram of the output section.

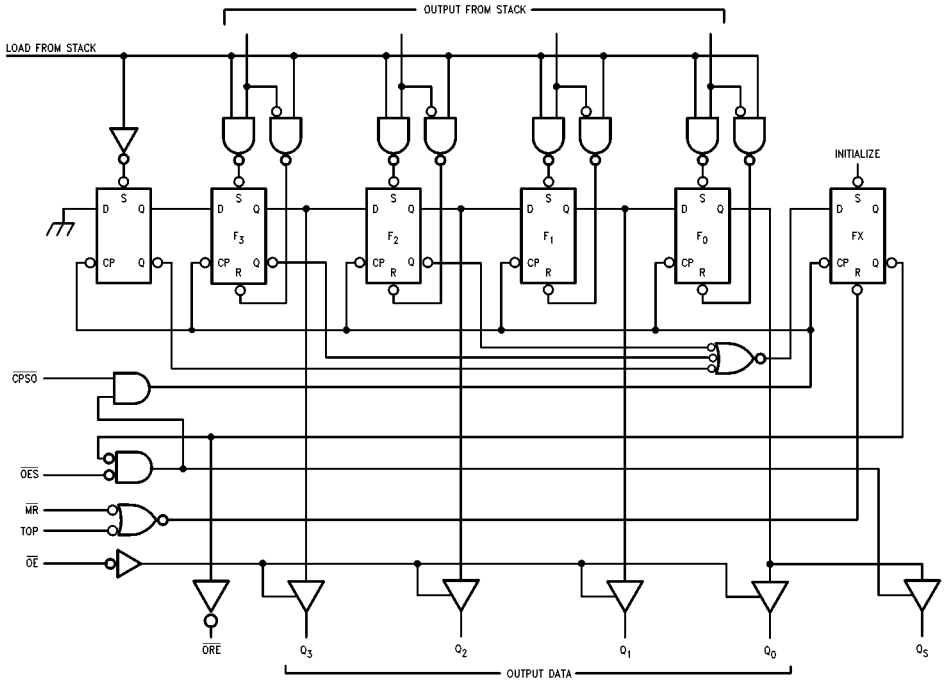


FIGURE 3. Conceptual Output Section

Parallel Data Extraction— When the FIFO is empty after a LOW pulse is applied to $\overline{MR}$, the Output Register Empty ($\overline{ORE}$) output is LOW. After data has been entered into the FIFO and has fallen through to the bottom stack location, it is transferred into the Output Register provided the "Transfer Out Parallel" (TOP) input is HIGH. As a result of the data transfer $\overline{ORE}$ goes HIGH, indicating valid data on the data outputs (provided the 3-STATE buffer is enabled). TOP can now be used to clock out the next word. When TOP goes LOW, $\overline{ORE}$ will go LOW indicating that the output data has been extracted, but the data itself remains on the output bus until the next HIGH level at TOP permits the transfer of the next word (if available) into the Output Register. During parallel data extraction $\overline{CPSO}$ should be LOW. TOS should be grounded for single slice operation or connected to the appropriate $\overline{ORE}$ for expanded operation (see Expansion section).

TOP is not edge triggered. Therefore, if TOP goes HIGH before data is available from the stack, but data does become available before TOP goes LOW again, that data will be transferred into the Output Register. However, internal control circuitry prevents the same data from being transferred twice. If TOP goes HIGH and returns to LOW before data is available from the stack, $\overline{ORE}$ remains LOW indicating that there is no valid data at the outputs.

Serial Data Extraction— When the FIFO is empty after a LOW pulse is applied to $\overline{MR}$, the Output Register empty ($\overline{ORE}$) output is LOW. After data has been entered into the FIFO and has fallen through to the bottom stack location, it is transferred into the Output Register provided TOS is LOW and TOP is HIGH. As a result of the data transfer $\overline{ORE}$ goes HIGH indicating valid data in the register. The 3-STATE Serial Data Output, Q_S, is automatically enabled and puts the first data bit on the output bus. Data is serially shifted out on the HIGH-to-LOW transition of $\overline{CPSO}$. To prevent false shifting, $\overline{CPSO}$ should be LOW when the new word is being loaded into the Output Register. The fourth transition empties the shift register, forces $\overline{ORE}$ output LOW and disables the serial output, Q_S (refer to Figure 3). For serial operation the $\overline{ORE}$ output may be tied to the $\overline{TOS}$ input, requesting a new word from the stack as soon as the previous one has been shifted out.

EXPANSION

Vertical Expansion— The 74F403A may be vertically expanded to store more words without external parts. The interconnection is necessary to form a 46-word by 4-bit FIFO are shown in Figure 4. Using the same technique, and FIFO of (15n + 1)-words by 4-bits can be constructed, where n is the number of devices. Note that expansion does not sacrifice any of the 74F403A's flexibility for serial/parallel input and output.

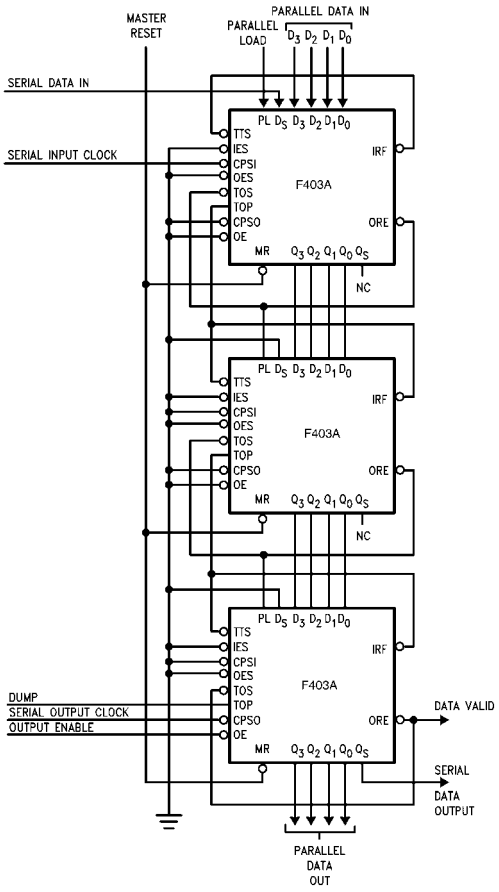


FIGURE 4. A Vertical Expansion Scheme

Horizontal and Vertical Expansion— The 74F403A can be expanded in both the horizontal and vertical directions without any external parts and without sacrificing any of its FIFO's flexibility for serial/parallel input and output. The interconnections necessary to form a 31-word by 16-bit FIFO are shown in Figure 6. Using the same technique, any FIFO of (15m + 1)-words by (4n)-bits can be constructed, where m is the number of devices in a column and n is the number of devices in a row. Figure 7 and Figure 8 show the timing diagrams for serial data entry and extraction for the 31-word by 16-bit FIFO shown in Figure 6. The final position of data after serial insertion of 496 bits into the FIFO array of Figure 6 is shown in Figure 9.

Interlocking Circuitry— Most conventional FIFO designs provide status signals analogous to $\overline{IRF}$ and $\overline{ORE}$. However, when these devices are operated in arrays, variations in unit to unit operating speed require external gating to assure all devices have completed an operation. The 74F403A incorporates simple but effective "master/slave" interlocking circuitry to eliminate the need for external gating.

In the 74F403A array of Figure 6 devices 1 and 5 are defined as "row masters" and the other devices are slaves to the master in their row. No slave in a given row will initialize its Input Register until it has received LOW on its $\overline{IES}$ input from a row master or a slave of higher priority.

In a similar fashion, the $\overline{ORE}$ outputs of slaves will not go HIGH until their $\overline{OES}$ inputs have gone HIGH.This interlocking scheme ensures that new input data may be accepted by the array when the $\overline{IRF}$ output of the final slave in that row goes HIGH and that output data for the array may be extracted when the $\overline{ORE}$ of the final slave in the output row goes HIGH.

The row master is established by connecting its $\overline{IES}$ input to ground while a slave receives its $\overline{IES}$ input from the $\overline{IRF}$ output of the next higher priority device. When an array of 74F403A FIFOs is initialized with a LOW on the $\overline{MR}$ inputs of all devices, the $\overline{IRF}$ outputs of all devices will be HIGH. Thus, only the row master receives a LOW on the $\overline{IES}$ input during initialization. Figure 10 is a conceptual logic diagram of the internal circuitry which determines master/slave operation. Whenever $\overline{MR}$ and $\overline{IES}$ are LOW, the Master Latch is set. Whenever $\overline{TTS}$ goes LOW the Request Initialization Flip-Flop will be set. If the Master Latch is HIGH, the Input Register will be immediately initialized and the Request Initialization Flip-Flop reset. If the Master Latch is reset, the Input Register is not initialized until $\overline{IES}$ goes LOW. In array operation, activating the $\overline{TTS}$ initiates a ripple input register initialization from the row master to the last slave.

A similar operation takes place for the output register. Either a $\overline{TOS}$ or TOP input initiates a load-from-stack operation and sets the $\overline{ORE}$ Request Flip-Flop. If the Master Latch is set, the last Output Register Flip-Flop is set and $\overline{ORE}$ goes HIGH. If the Master Latch is reset, the $\overline{ORE}$ output will be LOW until an $\overline{OES}$ input is received.

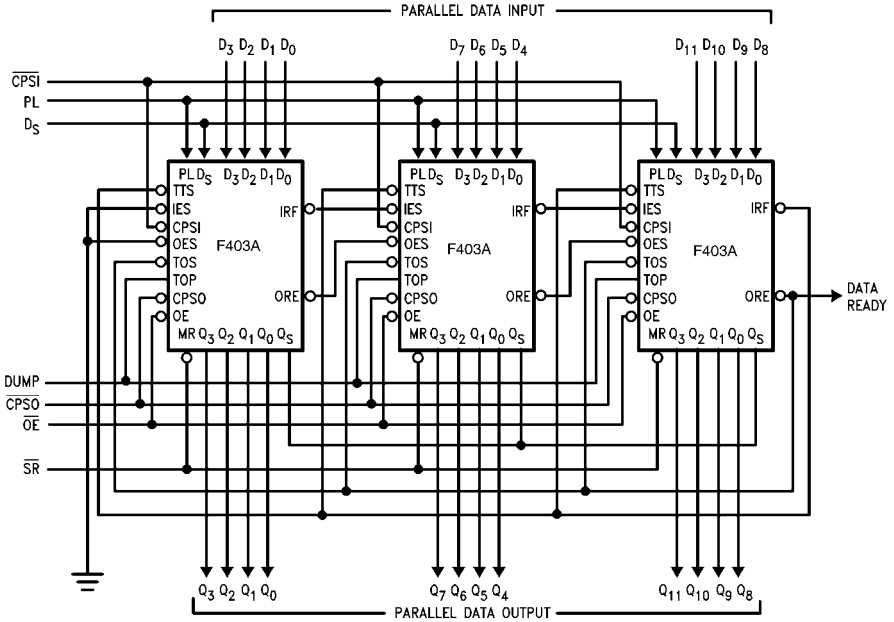


FIGURE 5. A Horizontal Expansion Scheme

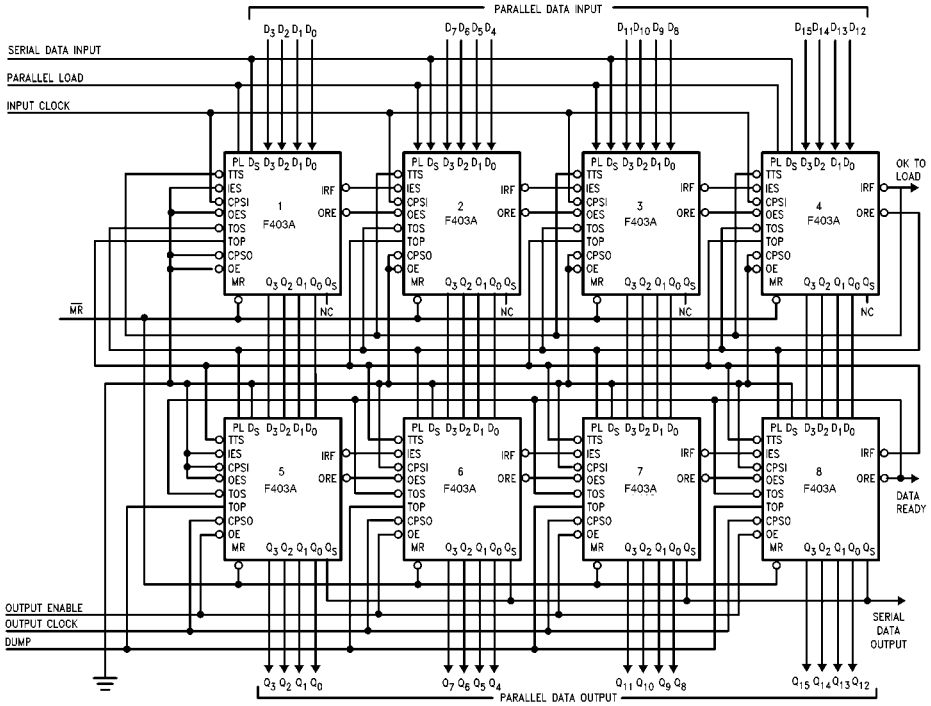


FIGURE 6. A 31 x 16 FIFO Array
GRAPHIC 00953610

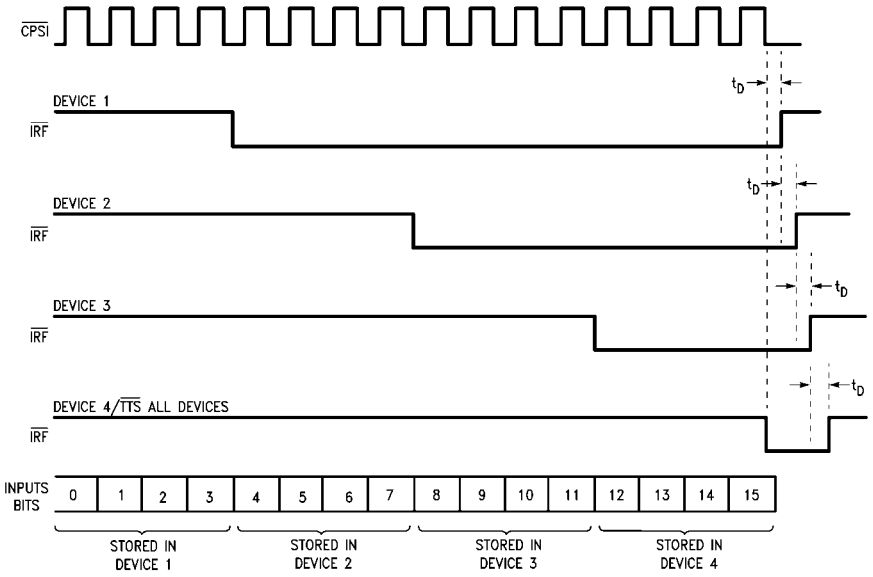


FIGURE 7. Serial Data Entry for Array of Figure 6

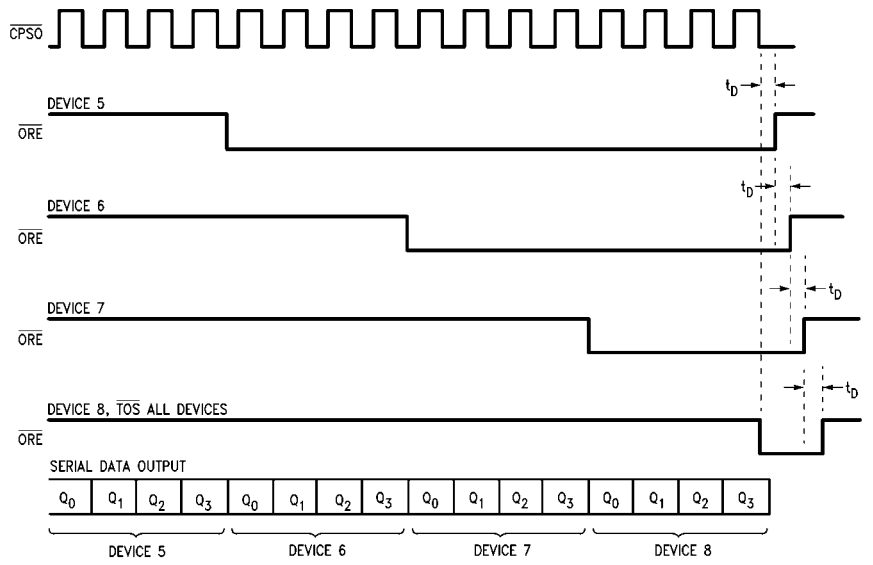


FIGURE 8. Serial Data Extraction for Array of Figure 6

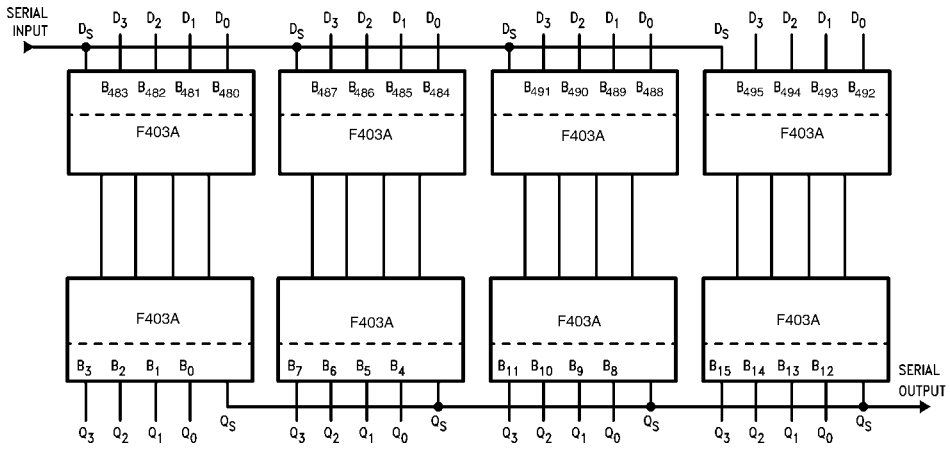


FIGURE 9. Final Position of a 496-Bit Serial Input

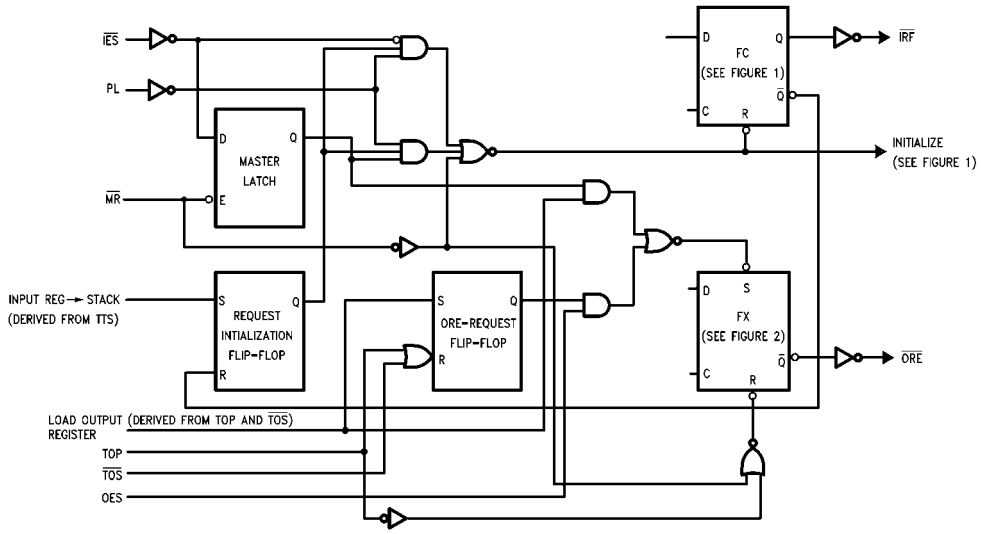


FIGURE 10. Conceptual Diagram, Interlocking Circuitry

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
In HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Type	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.5	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −400 µA ($\overline{IRF}$, $\overline{ORE}$)
		10% V_{CC}	2.5					I_{OH} = −5.7 mA (Q_n, Q_s)
		5% V_{CC}	2.7					I_{OH} = −400 µA ($\overline{IRF}$, $\overline{ORE}$)
		5% V_{CC}	2.7					I_{OH} = −5.7 mA (Q_n, Q_s)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 8 mA ($\overline{IRF}$, $\overline{ORE}$)
		10% V_{CC}			0.5			I_{OL} = 16 mA (Q_n, Q_s)
I_{IH}	Input HIGH Current				20	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−0.4	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−20		−130	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC}
I_{CCL}	Power Supply Current				170	mA	Max	V_0 = LOW

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units	Figure Number
		Min	Max	Min	Max		
t_{PHL}	Propagation Delay, Negative-Going $\overline{CPSI}$ to $\overline{IRF}$ Output	7.5	14.0	7.0	15.0	ns	Figure 11 Figure 12
t_{PLH}	Propagation Delay, Negative-Going $\overline{TTS}$ to $\overline{IRF}$	11.0	20.5	10.0	22.5		
t_{PLH} t_{PHL}	Propagation Delay, Negative-Going $\overline{CPSO}$ to Q_S Output	8.5 8.0	17.0 14.5	7.5 7.0	18.5 15.5	ns	Figure 13 Figure 14
t_{PLH} t_{PHL}	Propagation Delay, Positive-Going TOP to Outputs Q_0-Q_3	10.0 8.5	18.0 15.5	9.0 8.0	20.0 16.5	ns	Figure 15
t_{PHL}	Propagation Delay, Negative-Going $\overline{CPSO}$ to $\overline{ORE}$	9.5	17.5	9.0	19.0	ns	Figure 13 Figure 14
t_{PHL}	Propagation Delay, Negative-Going TOP to $\overline{ORE}$	8.0	15.0	7.5	16.5	ns	Figure 15
t_{PLH}	Propagation Delay, Positive-Going TOP or $\overline{ORE}$	12.5	22.0	11.5	25.0		
t_{PLH}	Propagation Delay, Negative-Going $\overline{TOS}$ to Positive Going $\overline{ORE}$	12.5	22.0	11.0	25.0	ns	Figure 13 Figure 14
t_{PHL}	Propagation Delay, Positive-Going PL to Negative-Going $\overline{IRF}$	7.0	13.0	6.5	14.0	ns	Figure 17 Figure 18
t_{PLH}	Propagation Delay, Negative-Going PL to Positive-Going $\overline{IRF}$	9.5	17.0	8.5	19.5		
t_{PLH}	Propagation Delay, Apostatize-Going $\overline{OES}$ to $\overline{ORE}$	10.0	18.0	9.0	20.5	ns	
t_{PLH}	Propagation Delay, Positive-Going IES to Positive-Going $\overline{IRF}$	8.5	15.5	7.5	17.5	ns	Figure 18
t_{PLH}	Propagation Delay, $\overline{MR}$ to $\overline{IRF}$	8.0	15.0	7.5	17.0	ns	
t_{PHL}	Propagation Delay, $\overline{MR}$ to $\overline{ORE}$	9.0	16.0	8.0	17.5	ns	
t_{PZH} t_{PZL}	Propagation Delay, $\overline{OE}$ to Q_0, Q_1, Q_2, Q_3	2.5 2.5	6.5 7.5	2.0 2.0	8.0 8.5	ns	
t_{PHZ} t_{PLZ}	Propagation Delay, $\overline{OE}$ to Q_0, Q_1, Q_2, Q_3	2.5 2.5	6.5 7.5	2.0 2.0	8.0 8.0		
t_{PZH} t_{PZL}	Propagation Delay, Negative-Going $\overline{OES}$ to Q_S	5.5 5.5	12.0 14.0	5.0 5.0	15.0 15.0	ns	
t_{PHZ} t_{PLZ}	Propagation Delay, Negative-Going $\overline{OES}$ to Q_S	5.5 5.5	12.0 14.5	5.0 5.0	14.0 16.0		

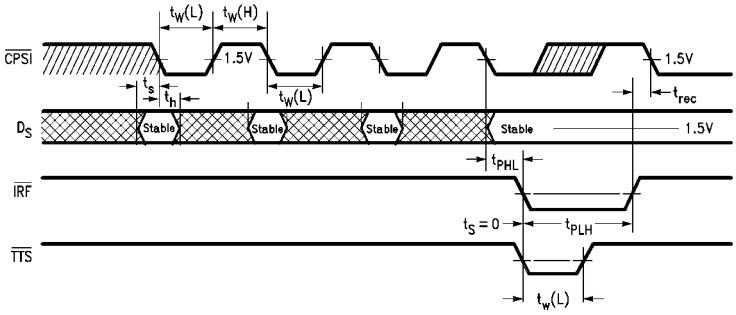
AC Electrical Characteristics (Continued)

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0° \text{ to } +70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units	Figure Number
		Min	Max	Min	Max		
t_{PZH}	Turn On Time	8.5	21.0	8.0	24.0	ns	
t_{PZL}	$\overline{TOS}$ to Q_S	8.5	20.0	8.0	21.0		
t_{DFT}	Fall Through Time	45.0	80.0	35.0	95.0	ns	Figure 16
t_{AP}	Parallel Appearance Time, $\overline{ORE}$ to Q_0-Q_3	−10.0	−1.0	−10.0	−1.0	ns	
t_{AS}	Serial Appearance Time, $\overline{ORE}$ to Q_S	−10.0	2.0	−10.0	20		

AC Operating Requirements

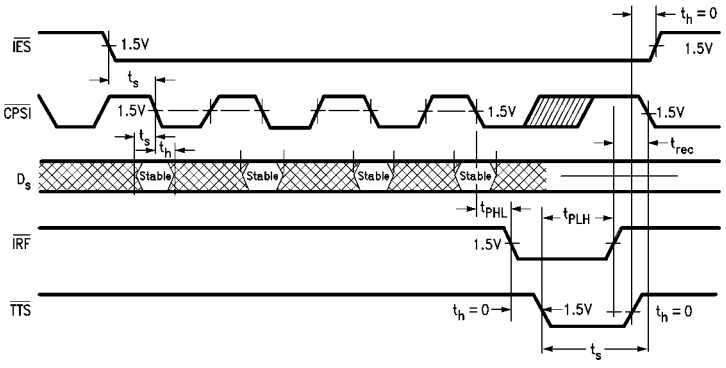
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C \text{ to } +70°C$, $V_{CC} = +5.0V$		Units	Figure Number
		Min	Max	Min	Max		
$t_S(H)$	Set-up Time HIGH or LOW	1.0		1.0		ns	Figure 11 Figure 12
$t_S(L)$	D_S to Negative $\overline{CPSI}$	1.0		1.0			
$t_H(H)$	Hold Time, HIGH or LOW	3.5		3.5			
$t_H(L)$	D_S to $\overline{CPSI}$	3.5		3.5			
$t_S(L)$	Set-up Time, LOW $\overline{TTS}$ to $\overline{IRF}$ Serial or Parallel Mode	0		0		ns	Figure 11 Figure 12 Figure 17 Figure 18
$t_S(L)$	Set-up Time, LOW Negative-Going $\overline{ORE}$ to Negative-Going $\overline{TOS}$	0		0		ns	Figure 13 Figure 14
$t_S(L)$	Set-up Time, LOW Negative-Going $\overline{IES}$ to $\overline{CPSI}$	3.0		4.0		ns	Figure 12
$t_S(L)$	Set-up Time, LOW Negative-Going $\overline{TTS}$ to $\overline{CPSI}$	14.0		15.5		ns	Figure 12
$t_S(H)$	Set-up Time, HIGH or LOW	0		0		ns	
$t_S(L)$	Parallel Inputs to PL	0		0			
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.5			
$t_H(L)$	Parallel Inputs to PL	2.0		2.5			
$t_W(H)$	$\overline{CPSI}$ Pulse Width	5.0		6.0		ns	Figure 11 Figure 12
$t_W(L)$	HIGH or LOW	3.0		5.0			
$t_W(H)$	PL Pulse Width, HIGH	4.0		5.0		ns	Figure 17 Figure 18
$t_W(L)$	$\overline{TTS}$ Pulse Width, LOW Serial or Parallel Mode	3.5		4.0		ns	Figure 11 Figure 12 Figure 13 Figure 14
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	3.5		4.0		ns	Figure 16
$t_W(H)$	TOP Pulse Width	4.5		5.5		ns	Figure 15
$t_W(L)$	HIGH or LOW	3.5		4.0			
$t_W(H)$	$\overline{CPSO}$ Pulse Width	4.5		5.5		ns	Figure 13 Figure 14
$t_W(L)$	HIGH or LOW	3.0		4.0			
t_{REC}	Recovery Time $\overline{MR}$ to Any Input	5.0		5.5		ns	Figure 16

Timing Waveforms



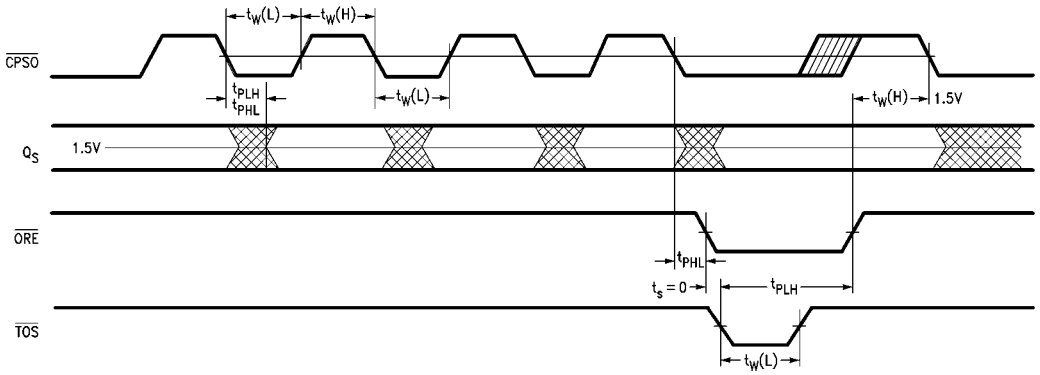
Conditions: stack not full, $\overline{IES}$, PL LOW

FIGURE 11. Serial Input, Unexpanded or Master Operation



Conditions: stack not full, $\overline{IES}$ HIGH when initiated, PL LOW

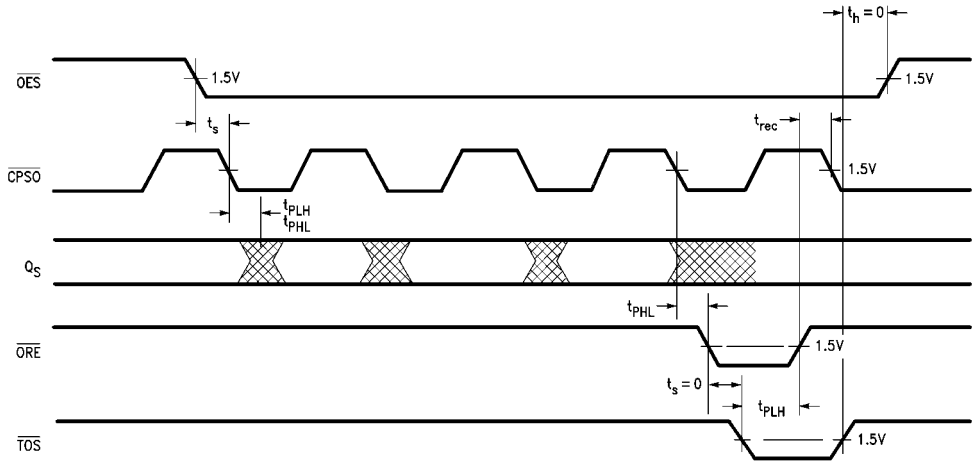
FIGURE 12. Serial Input, Expanded Slave Operation



Conditions: data in stack, TOP HIGH, $\overline{IES}$ LOW when initiated, $\overline{OES}$ LOW

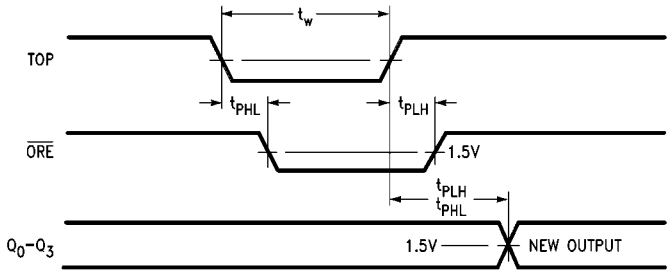
FIGURE 13. Serial Output, Unexpanded or Master Operation

Timing Waveforms (Continued)



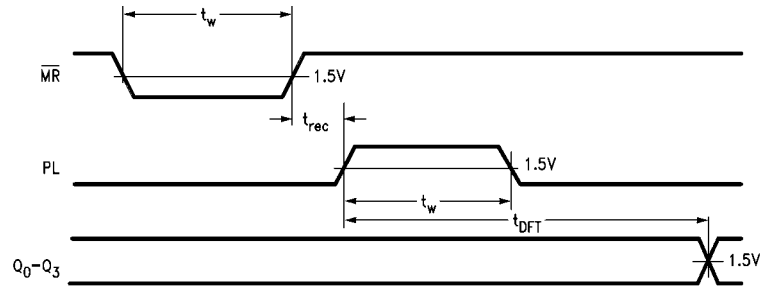
Conditions: data in stack, TOP HIGH, $\overline{IES}$ HIGH when initiated

FIGURE 14. Serial Output, Slave Operation



Conditions: $\overline{IES}$ LOW when initiated, $\overline{OE}$, $\overline{CPSO}$ LOW; data available in stack

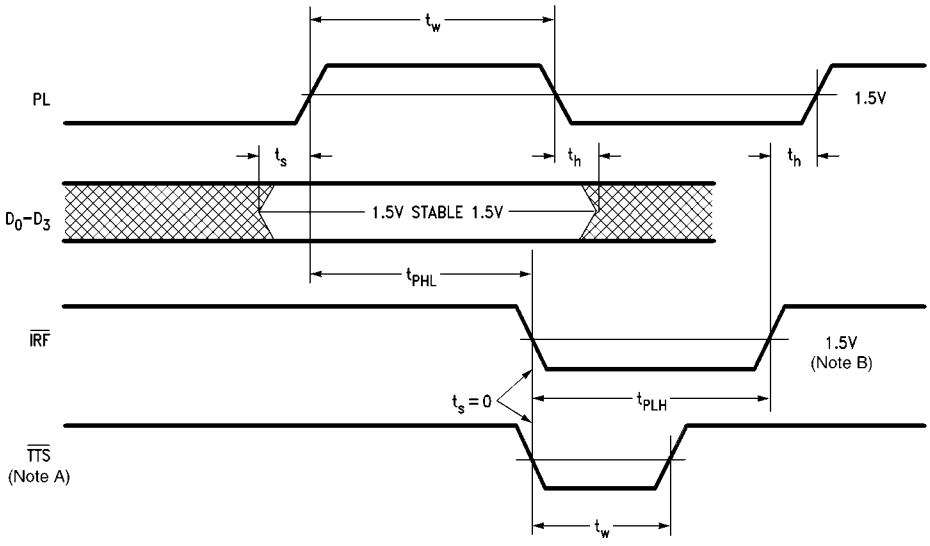
FIGURE 15. Parallel Output, 4-Bit Word or Master in Parallel Expansion



Conditions: $\overline{TTS}$ connected to $\overline{IRF}$, $\overline{TOS}$ connected to $\overline{ORE}$, $\overline{IES}$, $\overline{OES}$, $\overline{OE}$, $\overline{CPSO}$ LOW, TOP HIGH

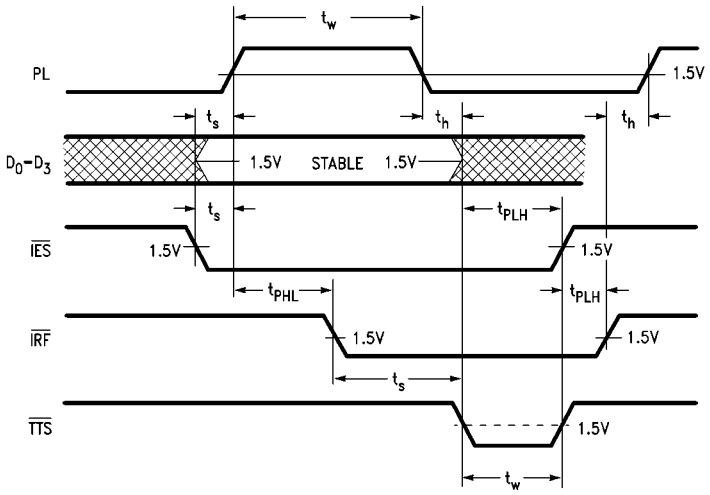
FIGURE 16. Fall Through Time

Timing Waveforms (Continued)



Conditions: stack not full, $\overline{IES}$ LOW when initialized
NOTE A: $\overline{TTS}$ normally connected to $\overline{IRF}$.
NOTE B: If stack is full, $\overline{IRF}$ will stay LOW.

FIGURE 17. Parallel Load Mode, 4-Bit Word (Unexpanded) or Master in Parallel Expansion

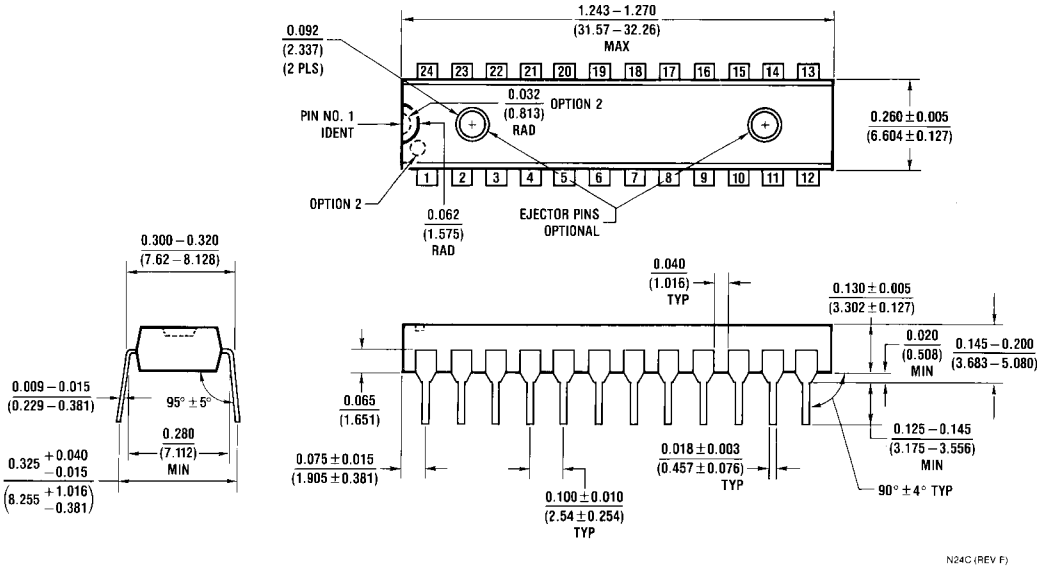


Conditions: stack not full, device initialized (Note 3) with $\overline{IES}$ HIGH

FIGURE 18. Parallel Load, Slave Mode

Note 3: Initialization requires a master reset to occur after power has been applied.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

August 1995

54F/74F410 Register Stack—16 x 4 RAM TRI-STATE® Output Register

General Description

The 'F410 is a register-oriented high-speed 64-bit Read/Write Memory organized as 16-words by 4-bits. An edge-triggered 4-bit output register allows new input data to be written while previous data is held. TRI-STATE outputs are provided for maximum versatility. The 'F410 is fully compatible with all TTL families.

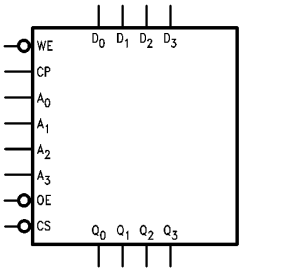
Features

- Edge-triggered output register
- Typical access time of 35 ns
- TRI-STATE outputs
- Optimized for register stack operation
- 18-pin package
- 9410 replacement

Commercial	Military	Package Number	Package Description
74F410PC		N18A	18-Lead (0.300″ Wide) Molded Dual-In-Line
	54F410DM (Note 1)	J18A	18-Lead Ceramic Dual-In-Line
74F410SC		M20B	20-Lead (0.300″ Wide) Molded Small Outline, JEDEC
54F410LM		W20A	20-Lead Cerpak

Note 1: Military grade device with environmental and burn-in processing. Use suffix = DMQB, LMQB

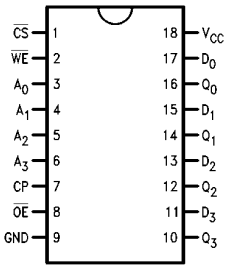
Logic Symbol



TL/F/9538–3

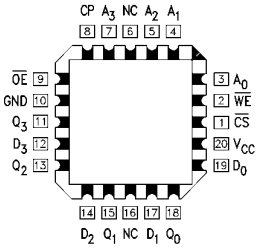
Connection Diagrams

Pin Assignment for DIP and SOIC



TL/F/9538–1

Pin Assignment for LCC



TL/F/9538–2

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Unit Loading/Fan Out

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0-A_3	Address Inputs	1.0/1.0	20 μA/ $-$0.6 mA
D_0-D_3	Data Inputs	1.0/1.0	20 μA/ $-$0.6 mA
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/2.0	20 μA/ $-$1.2 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/ $-$0.6 mA
$\overline{WE}$	Write Enable Input (Active LOW)	1.0/1.0	20 μA/ $-$0.6 mA
CP	Clock Input (Outputs Change on LOW-to-HIGH Transition)	1.0/2.0	20 μA/ $-$1.2 mA
Q_0-Q_3	TRI-STATE Outputs	150/40 (33.3)	$-$3 mA/24 mA (20 mA)

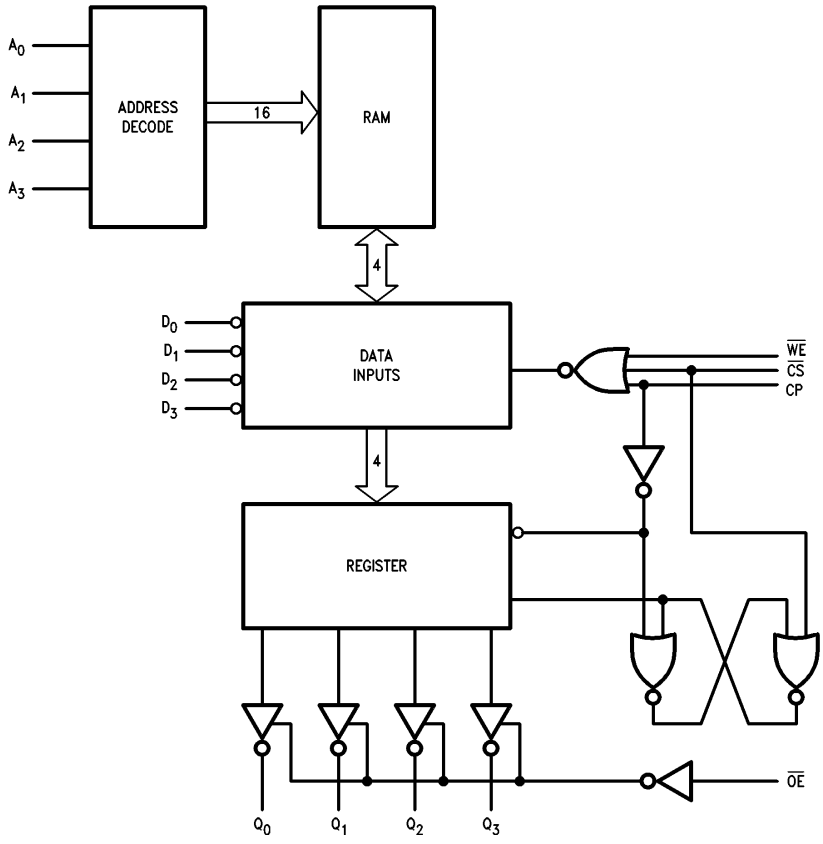
Functional Description

Write Operation—When the three control inputs, Write Enable ($\overline{WE}$), Chip Select ($\overline{CS}$), and Clock (CP), are LOW the information on the data inputs (D_0-D_3) is written into the memory location selected by the address inputs (A_0-A_3). If the input data changes while $\overline{WE}$, $\overline{CS}$, and CP are LOW, the contents of the selected memory location follow these changes, provided setup and hold time criteria are met.

Read Operation—Whenever $\overline{CS}$ is LOW and CP goes from LOW-to-HIGH, the contents of the memory location selected by the address inputs (A_0-A_3) are edge-triggered into the Output Register.

The ($\overline{OE}$) input controls the output buffers. When $\overline{OE}$ is HIGH the four outputs (Q_0-Q_3) are in a high impedance or OFF state; when $\overline{OE}$ is LOW, the outputs are determined by the state of the Output Register.

Block Diagram



TL/F/9538–4

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F Min	54F/74F Typ	54F/74F Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54F 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		54F 10% V_{CC}	2.4					I_{OH} = −3 mA
		74F 10% V_{CC}	2.5					I_{OH} = −1 mA
		74F 10% V_{CC}	2.4					I_{OH} = −3 mA
		74F 5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	54F 10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
		74F 10% V_{CC}			0.5			I_{OL} = 24 mA
I_{IH}	Input HIGH Current	54F			20.0	μA	Max	V_{IN} = 2.7V
		74F			5.0			
I_{BVI}	Input HIGH Current Breakdown Test	54F			100	μA	Max	V_{IN} = 7.0V
		74F			7.0			
I_{CEX}	Output HIGH Leakage Current	54F			250	μA	Max	V_{OUT} = V_{CC}
		74F			50			
V_{ID}	Input Leakage Test	74F	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current	74F			3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (A_n, D_n, $\overline{OE}$, $\overline{WE}$)
					−1.2			V_{IN} = 0.5V ($\overline{CS}$, CP)
I_{OZH}	Output Leakage Current				50	μA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	μA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	μA	0.0V	V_{OUT} = 5.25V

DC Electrical Characteristics (Continued)

Symbol	Parameter	54F/74F			Units	V_{CC}	Conditions
		Min	Typ	Max			
I_{CCH}	Power Supply Current		47	70	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		47	70	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		47	70	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	74F T_A = +25°C V_{CC} = +5.0V C_L = 50 pF		54F T_A, V_{CC} = Mil C_L = 50 pF		74F T_A, V_{CC} = Com C_L = 50 pF		Units
		Min	Max	Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay CP to Q	3.0 3.5	8.5 9.0	2.5 3.0	11.0 12.0	2.5 3.0	9.5 10.0	ns
t_{PZH} t_{PZL}	Enable Time $\overline{OE}$ to Q	3.0 3.5	8.0 9.0	2.5 3.0	10.5 13.0	2.5 3.0	9.0 10.0	ns
t_{PHZ} t_{PLZ}	Disable Time $\overline{OE}$ to Q	2.5 2.5	6.5 7.0	2.0 2.0	8.5 9.5	2.0 2.0	7.5 8.0	

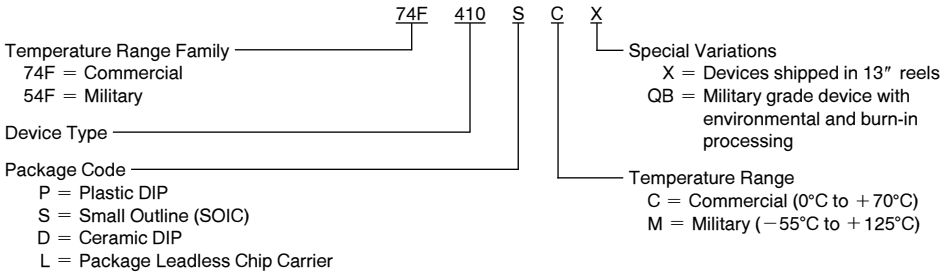
AC Operating Requirements

Symbol	Parameter	74F T_A = +25°C V_{CC} = +5.0V		54F T_A, V_{CC} = Mil		74F T_A, V_{CC} = Com		Units
		Min	Max	Min	Max	Min	Max	
READ MODE								
t_s(H) t_s(L)	Setup Time, HIGH or LOW A_n to CP	15.0 15.0		23 23		17.0 17.0		ns
t_h(H) t_h(L)	Hold Time, HIGH or LOW A_n to CP	0 0		0 0		0 0		ns
WRITE MODE								
t_s(H) t_s(L)	Setup Time, HIGH or LOW A_n to $\overline{WE}$	0 0		0 0		0 0		ns
t_h(H) t_h(L)	Hold Time, HIGH or LOW A_n to $\overline{WE}$	0 0		0 0		0 0		ns
t_s(H) t_s(L)	Setup Time, HIGH or LOW D_n to $\overline{WE}$	5.0 5.0		8.5 8.5		6.0 6.0		ns
t_h(H) t_h(L)	Hold Time, HIGH or LOW D_n to $\overline{WE}$	0 0		2.5 2.5		0 0		ns
t_w	$\overline{WE}$ Pulse Width Required to Write	7.5		9.5		8.5		ns
t_w	$\overline{CS}$ Pulse Width Required to Write	7.5		9.5		8.5		ns
t_w	CP Pulse Width Required to Write	7.5		9.5		8.5		ns

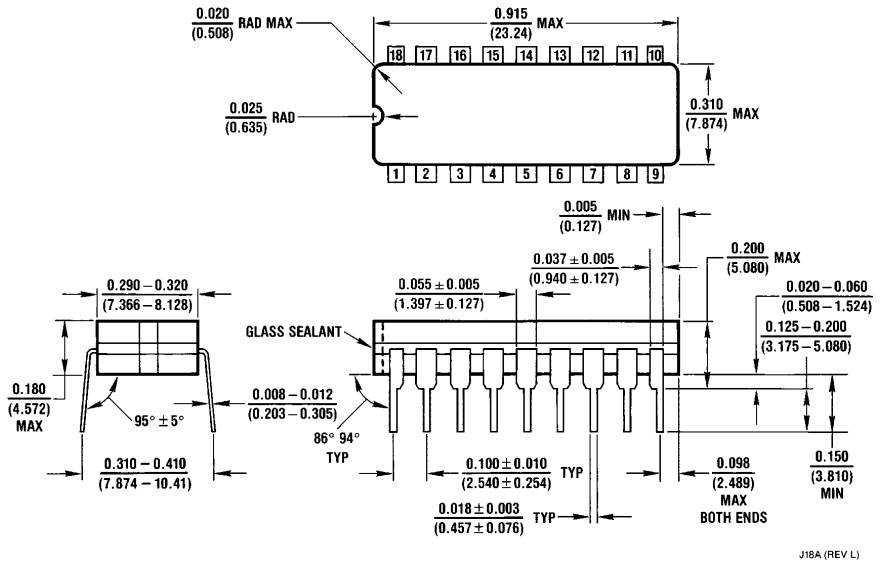
Note: Military temperature range for this device is −40°C to +85°C.

Ordering Information

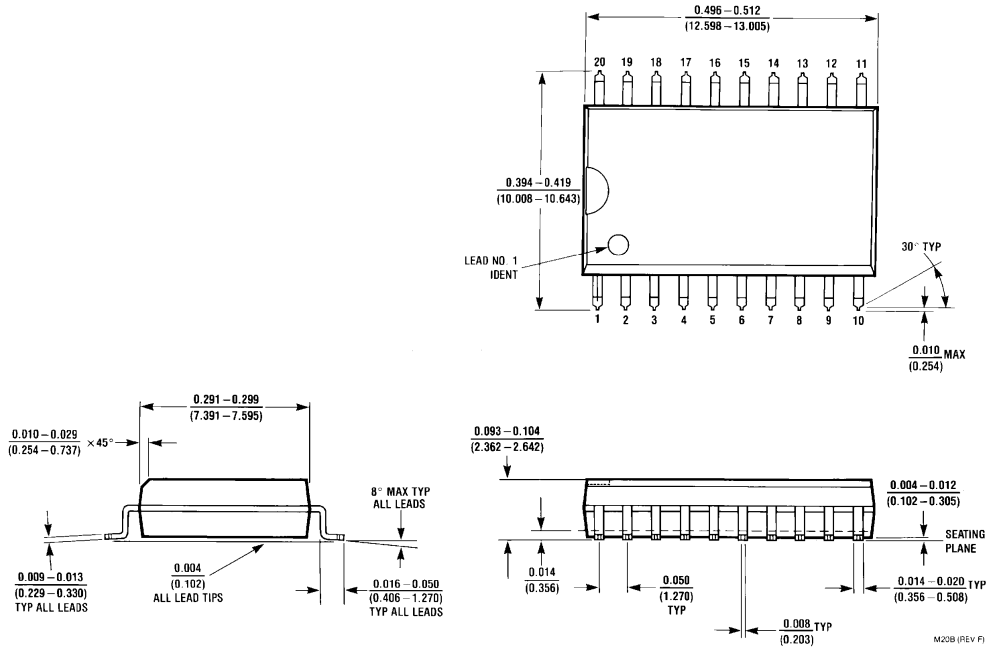
The device number is used to form part of a simplified purchasing code where a package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)

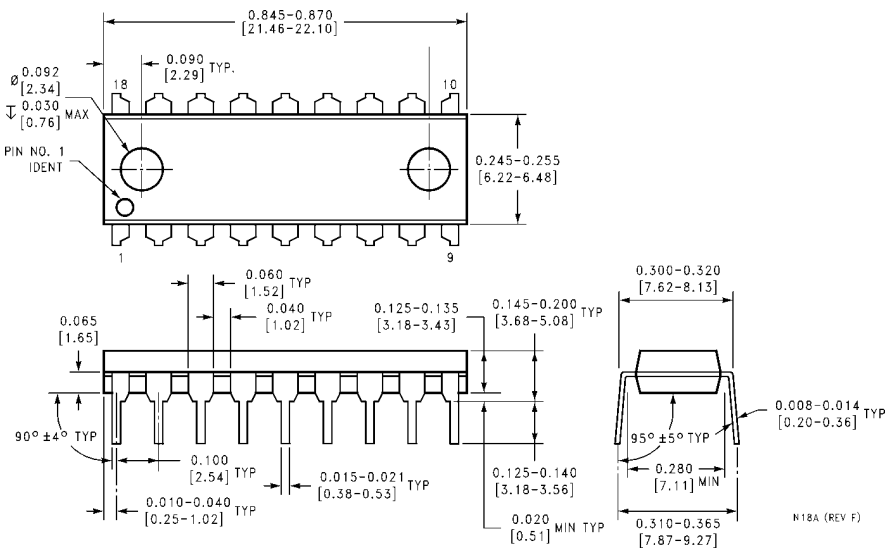


18-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J18A



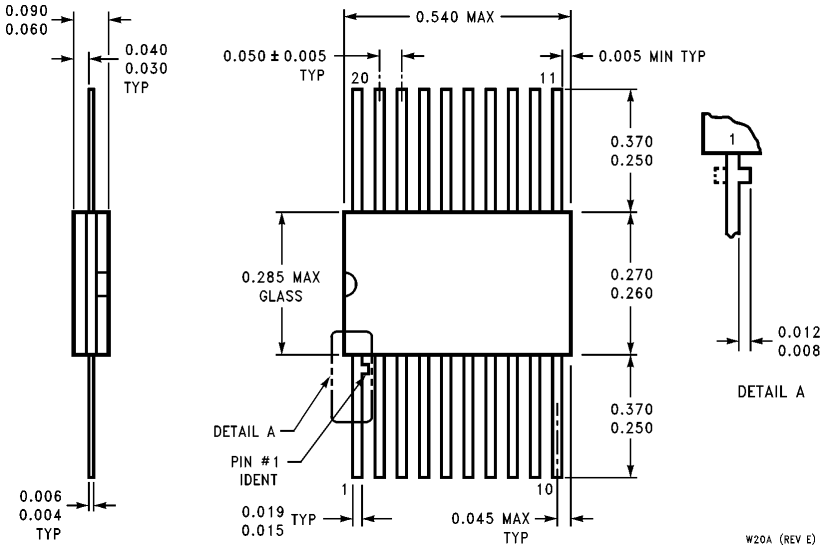
20-Lead (0.300″ Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M20B

Physical Dimensions inches (millimeters) (Continued)



18-Lead (0.300″ Wide) Molded Dual-In-Line Package (P)
NS Package Number N18A

Physical Dimensions inches (millimeters) (Continued)



20-Lead Cerpack
NS Package Number W20A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F413
64 x 4 First-In First-Out Buffer Memory with Parallel I/O

General Description

The F413 is an expandable fall-through type high-speed First-In First-Out (FIFO) buffer memory organized as 64 words by four bits. The 4-bit input and output registers record and transmit, respectively, asynchronous data in parallel form. Control pins on the input and output allow for handshaking and expansion. The 4-bit wide, 62-bit deep fall-through stack has self-contained control logic.

Features

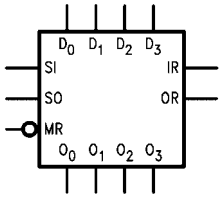
- Separate input and output clocks
- Parallel input and output
- Expandable without external logic
- 15 MHz data rate
- Supply current 160 mA max
- Available in SOIC, (300 mil only)

Ordering Code:

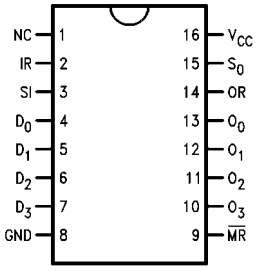
Order Number	Package Number	Package Description
74F413PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_3	Data Inputs	1.0/0.667	20 µA/–0.4 mA
O_0–O_3	Data Outputs	50/13.3	–1 mA/8 mA
IR	Input Ready	1.0/0.667	20 µA/–0.4 mA
SI	Shift In	1.0/0.667	20 µA/–0.4 mA
SO	Shift Out	1.0/0.667	20 µA/–0.4 mA
OR	Output Ready	1.0/0.667	20 µA/–0.4 mA
$\overline{MR}$	Master Reset	1.0/0.667	20 µA/–0.4 mA

Functional Description

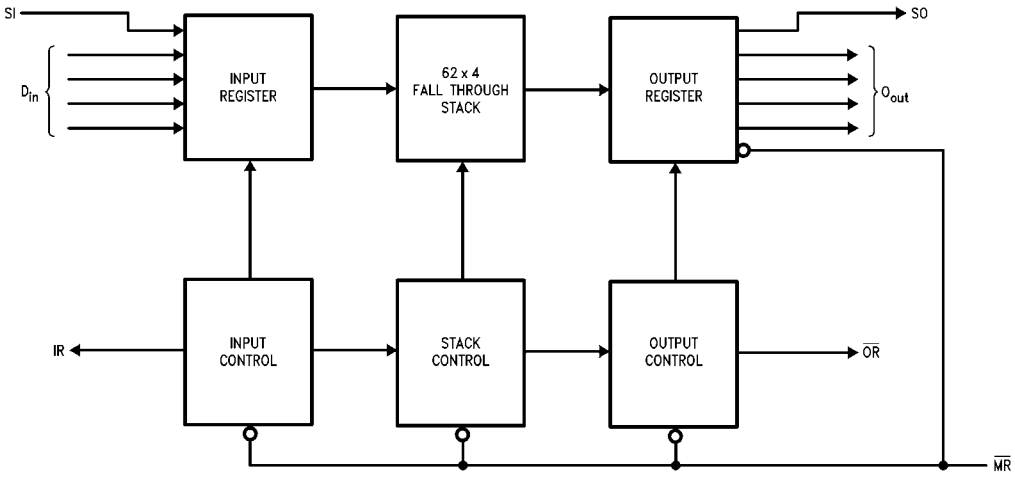
Data Input— Data is entered into the FIFO on D_0–D_3 inputs. To enter data the Input Ready (IR) should be HIGH, indicating that the first location is ready to accept data. Data then present at the four data inputs is entered into the first location when the Shift In (SI) is brought HIGH. An SI HIGH signal causes the IR to go LOW. Data remains at the first location until SI is brought LOW. When SI is brought LOW and the FIFO is not full, IR will go HIGH, indicating that more room is available. Simultaneously, data will propagate to the second location and continue shifting until it reaches the output stage or a full location. If the memory is full, IR will remain LOW.

Data Transfer— Once data is entered into the second cell, the transfer of any full cell to the adjacent (downstream) empty cell is automatic, activated by an on-chip control. Thus data will stack up at the end of the device while empty locations will "bubble" to the front. The t_{PT} parameter defines the time required for the first data to travel from input to the output of a previously empty device.

Data Output— Data is read from the O_0–O_3 outputs. When data is shifted to the output stage, Output Ready (OR) goes HIGH, indicating the presence of valid data. When the OR is HIGH, data may be shifted out by bringing the Shift Out (SO) HIGH. A HIGH signal at SO causes the OR to go LOW. Valid data is maintained while the SO is HIGH. When SO is brought LOW, the upstream data, provided that stage has valid data, is shifted to the output stage. When new valid data is shifted to the output stage, OR goes HIGH. If the FIFO is emptied, OR stays LOW, and O_0–O_3 remains as before, i.e., data does not change if FIFO is empty.

Input Ready and Output Ready— may also be used as status signals indicating that the FIFO is completely full (Input Ready stays LOW for at least t_{PT}) or completely empty (Output Ready stays LOW for at least t_{PT}).

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.5	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 8 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.4	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−20		−130	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			115	160	mA	Max	V_O = HIGH

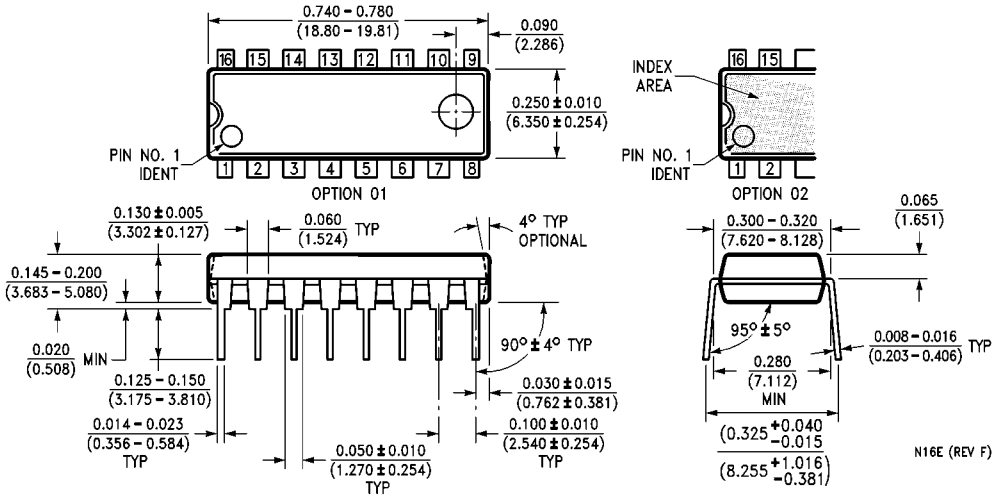
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Shift In Rate	10			8.0		10		MHz
f_{MAX}	Shift Out Rate	10			8.0		10		MHz
t_{PLH}	Propagation Delay	1.5		44.0	1.5	50.0	1.5	48.0	ns
t_{PHL}	Shift In to IR	1.5		31.0	1.5	37.0	1.5	35.0	
t_{PLH}	Propagation Delay	1.5		52.0	1.5	57.0	1.5	55.0	ns
t_{PHL}	Shift Out to OR	1.5		31.0	1.5	37.0	1.5	35.0	
t_{PLH}	Propagation Delay	1.5		46.0	1.5	52.0	1.5	50.0	ns
t_{PHL}	Output Data Delay	1.5		34.0	1.5	39.0	1.5	37.0	
t_{PLH}	Propagation Delay Master Reset to IR	1.5		27.0	1.5	33.0	1.5	31.0	ns
t_{PLH}	Propagation Delay Master Reset to OR	1.5		30.0	1.5	34.0	1.5	32.0	ns

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	1.0		1.0		1.0		ns
$t_S(L)$	D_n to SI	1.0		1.0		1.0		
$t_H(H)$	Hold Time, HIGH or LOW	10.0		10.0		10.0		
$t_H(L)$	D_n to SI	10.0		10.0		10.0		
$t_W(H)$	Shift In Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	10.0		10.0		10.0		
$t_W(H)$	Shift Out Pulse Width	7.5		8.5		7.5		
$t_W(L)$	HIGH or LOW	10.0		10.0		10.0		
$t_W(H)$	Input Ready Pulse Width, HIGH	7.5		8.5		7.5		ns
$t_W(L)$	Output Ready Pulse Width, LOW	5.0		5.0		5.0		ns
$t_W(L)$	Master Reset Pulse Width, LOW	10.0		10.0		10.0		ns
t_{REC}	Recovery Time, MR to SI	32.0		35.0		35.0		ns
t_{PT}	Data Throughput Time		0.9		1.0		1.0	µs

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F433
First-In First-Out (FIFO) Buffer Memory

General Description

The 74F433 is an expandable fall-through type high-speed First-In First-Out (FIFO) Buffer Memory that is optimized for high-speed disk or tape controller and communication buffer applications. It is organized as 64-words by 4-bits and may be expanded to any number of words or any number of bits in multiples of four. Data may be entered or extracted asynchronously in serial or parallel, allowing economical implementation of buffer memories.

The 74F433 has 3-STATE outputs that provide added versatility, and is fully compatible with all TTL families.

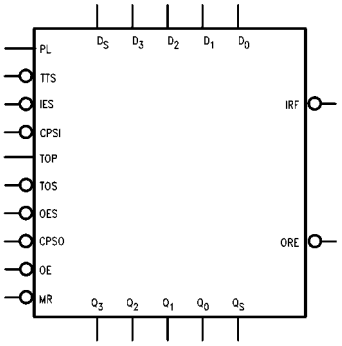
Features

- Serial or parallel input
- Serial or parallel output
- Expandable without additional logic
- 3-STATE outputs
- Fully compatible with all TTL families
- Slim 24-pin package
- 9423 replacement

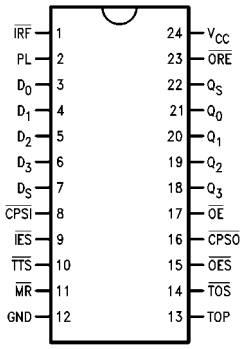
Ordering Code:

Order Number	Package Number	Package Description
74F433SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Logic Symbol



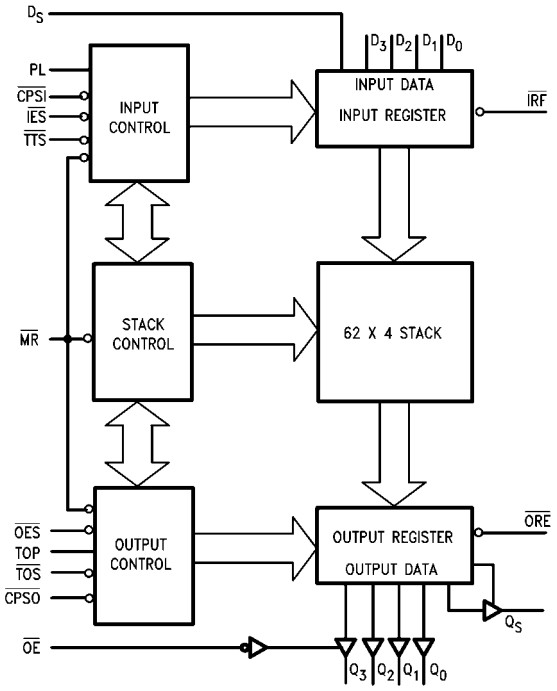
Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
PL	Parallel Load Input	1.0/0.66	20 µA/400 µA
$\overline{CPSI}$	Serial Input Clock	1.0/0.66	20 µA/400 µA
$\overline{IES}$	Serial Input Enable	1.0/0.66	20 µA/400 µA
$\overline{TTS}$	Transfer to Stack Input	1.0/0.66	20 µA/400 µA
$\overline{MR}$	Master Reset	1.0/0.66	20 µA/400 µA
$\overline{OES}$	Serial Output Enable	1.0/0.66	20 µA/400 µA
TOP	Transfer Out Parallel	1.0/0.66	20 µA/400 µA
$\overline{TOS}$	Transfer Out Serial	1.0/0.66	20 µA/400 µA
$\overline{CPSO}$	Serial Output Clock	1.0/0.66	20 µA/400 µA
$\overline{OE}$	Output Enable	1.0/0.66	20 µA/400 µA
D_0–D_3	Parallel Data Inputs	1.0/0.66	20 µA/400 µA
D_S	Serial Data Input	1.0/0.66	20 µA/400 µA
Q_0–Q_3	Parallel Data Outputs	285/10	5.7 mA/16 mA
Q_S	Serial Data Output	285/10	5.7 µA/16 mA
$\overline{IRF}$	Input Register Full	20/5	400 µA/8 mA
$\overline{ORE}$	Output Register Empty	20/5	400 µA/8 mA

Block Diagram



Functional Description

As shown in the block diagram, the 74F433 consists of three sections:

1. An Input Register with parallel and serial data inputs, as well as control inputs and outputs for input handshaking and expansion.
2. A 4-bit-wide, 62-word-deep fall-through stack with self-contained control logic.
3. An Output Register with parallel and serial data outputs, as well as control inputs and outputs for output handshaking and expansion.

These three sections operate asynchronously and are virtually independent of one another.

Input Register (Data Entry)

The Input Register can receive data in either bit-serial or 4-bit parallel form. It stores this data until it is sent to the fall-through stack, and also generates the necessary status and control signals.

This 5-bit register (see Figure 1) is initialized by setting flip-flop F_3 and resetting the other flip-flops. The $\overline{Q}$-output of the last flip-flop (FC) is brought out as the Input Register Full (IRF) signal. After initialization, this output is HIGH.

Parallel Entry—A HIGH on the Parallel Load (PL) input loads the D_0–D_3 inputs into the F_0–F_3 flip-flops and sets the FC flip-flop. This forces the $\overline{IRF}$ output LOW, indicating that the input register is full. During parallel entry, the Serial Input Clock ($\overline{CPSI}$) input must be LOW.

Serial Entry—Data on the Serial Data (D_S) input is serially entered into the shift register (F_3, F_2, F_1, F_0, FC) on each HIGH-to-LOW transition of the $\overline{CPSI}$ input when the Serial Input Enable ($\overline{IES}$) signal is LOW. During serial entry, the PL input should be LOW.

After the fourth clock transition, the four data bits are located in flip-flops F_0–F_3. The FC flip-flop is set, forcing the $\overline{IRF}$ output LOW and internally inhibiting $\overline{CPSI}$ pulses from affecting the register. Figure 2 illustrates the final positions in an 74F433 resulting from a 256-bit serial bit train (B_0 is the first bit, B_{255} the last).

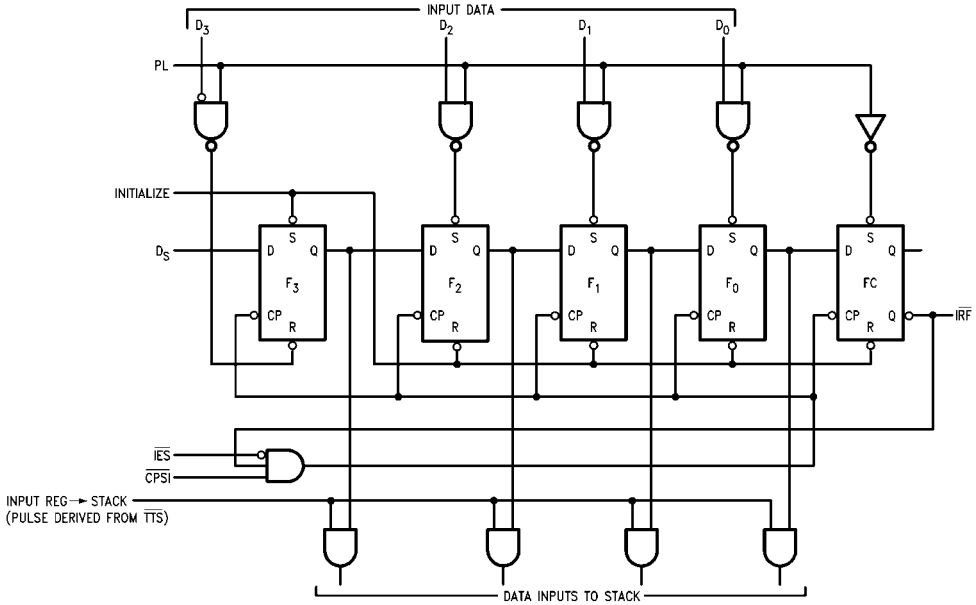


FIGURE 1. Conceptual Input Section

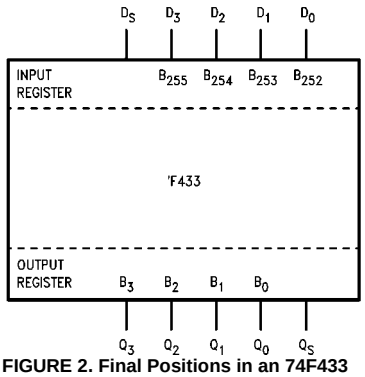


FIGURE 2. Final Positions in an 74F433 Resulting from a 256-Bit Serial Train

Fall-Through Stack—The outputs of flip-flops F_0–F_3 feed the stack. A LOW level on the Transfer to Stack ($\overline{TTS}$) input initiates a fall-through action; if the top location of the stack is empty, data is loaded into the stack and the input register is re-initialized. (Note that this initialization is delayed until PL is LOW). Thus, automatic FIFO action is achieved by connecting the $\overline{IRF}$ output to the $\overline{TTS}$ input.

An RS-type flip-flop (the initialization flip-flop) in the control section records the fact that data has been transferred to the stack. This prevents multiple entry of the same word into the stack even though $\overline{IRF}$ and $\overline{TTS}$ may still be LOW; the initialization flip-flop is not cleared until PL goes LOW.

Once in the stack, data falls through automatically, pausing only when it is necessary to wait for an empty next location. In the 74F433, the master reset ($\overline{MR}$) input only initializes the stack control section and does not clear the data.

Output Register

The Output Register (see Figure 3) receives 4-bit data words from the bottom stack location, stores them, and outputs data on a 3-STATE, 4-bit parallel data bus or on a 3-STATE serial data bus. The output section generates and receives the necessary status and control signals.

Parallel Extraction—When the FIFO is empty after a LOW pulse is applied to the MR input, the Output Register Empty ($\overline{ORE}$) output is LOW. After data has been entered into the FIFO and has fallen through to the bottom stack location, it is transferred into the output register, if the Transfer Out Parallel (TOP) input is HIGH. As a result of the data transfer, $\overline{ORE}$ goes HIGH, indicating valid data on the data outputs (provided that the 3-STATE buffer is enabled). The TOP input can then be used to clock out the next word.

When TOP goes LOW, $\overline{ORE}$ also goes LOW, indicating that the output data has been extracted; however, the data itself remains on the output bus until a HIGH level on TOP permits the transfer of the next word (if available) into the output register. During parallel data extraction, the serial output clock ($\overline{CPSO}$) line should be LOW. The Transfer Out Serial ($\overline{TOS}$) line should be grounded for single-slice operation or connected to the appropriate $\overline{ORE}$ line for expanded operation (refer to the "Expansion" section).

The TOP signal is not edge-triggered. Therefore, if TOP goes HIGH before data is available from the stack but data becomes available before TOP again goes LOW, that data is transferred into the output register. However, internal control circuitry prevents the same data from being transferred twice. If TOP goes HIGH and returns to LOW before data is available from the stack, $\overline{ORE}$ remains LOW, indicating that there is no valid data at the outputs.

Serial Extraction—When the FIFO is empty after a LOW is applied to the MR input, the $\overline{ORE}$ output is LOW. After data has been entered into the FIFO and has fallen through to the bottom stack location, it is transferred into the output register, if the $\overline{TOS}$ input is LOW and TOP is HIGH. As a result of the data transfer, $\overline{ORE}$ goes HIGH, indicating that valid data is in the register.

The 3-STATE Serial Data Output (Q_S) is automatically enabled and puts the first data bit on the output bus. Data is serially shifted out on the HIGH-to-LOW transition of $\overline{CPSO}$. To prevent false shifting, $\overline{CPSO}$ should be LOW when the new word is being loaded into the output register. The fourth transition empties the shift register, forces $\overline{ORE}$ LOW, and disables the serial output, Q_S. For serial operation, the $\overline{ORE}$ output may be tied to the $\overline{TOS}$ input, requesting a new word from the stack as soon as the previous one has been shifted out.

Expansion

Vertical Expansion—The 74F433 may be vertically expanded, without external components, to store more words. The interconnections necessary to form a 190-word by 4-bit FIFO are shown in Figure 4. Using the same technique, any FIFO of (63n+1)-words by 4-bits can be configured, where n is the number of devices. Note that expansion does not sacrifice any of the 74F433 flexibility for serial/parallel input and output.

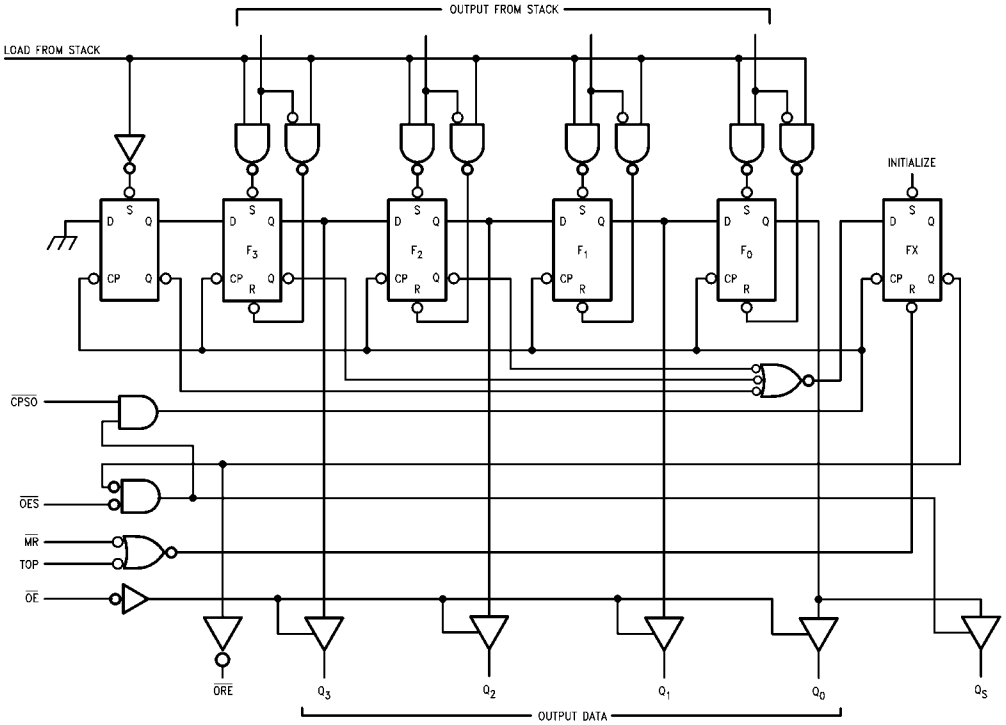


FIGURE 3. Conceptual Output Section

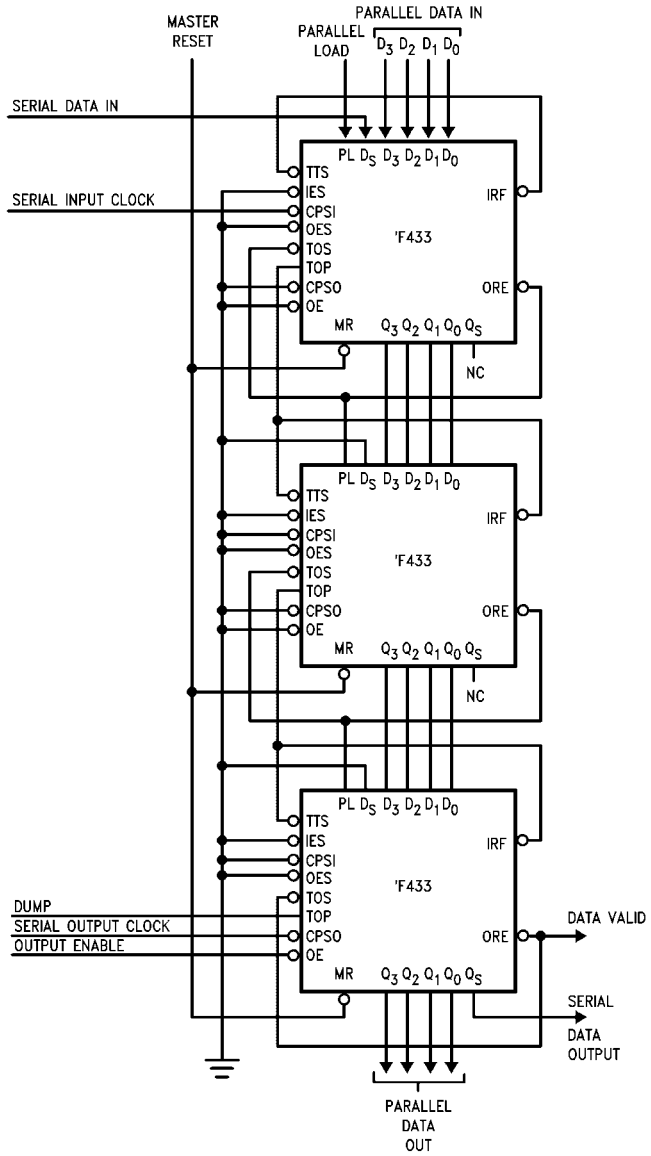


FIGURE 4. A Vertical Expansion Scheme

Horizontal Expansion—The 74F433 can be horizontally expanded, without external logic, to store long words (in multiples of 4-bits). The interconnections necessary to form a 64-word by 12-bit FIFO are shown in Figure 5. Using the same technique, any FIFO of 64-words by 4n-bits can be constructed, where n is the number of devices.

The right-most (most significant) device is connected to the $\overline{\text{TTS}}$ inputs of all devices. Similarly, the $\overline{\text{ORE}}$ output of the most significant device is connected to the $\overline{\text{TOS}}$ inputs of all devices. As in the vertical expansion scheme, horizontal expansion does not sacrifice any of the 74F433 flexibility for serial/parallel input and output.

It should be noted that the horizontal expansion scheme shown in Figure 5 exacts a penalty in speed.

Horizontal and Vertical Expansion—The 74F433 can be expanded in both the horizontal and vertical directions without any external components and without sacrificing any of its FIFO flexibility for serial/parallel input and output. The interconnections necessary to form a 127-word by 16-bit FIFO are shown in Figure 6. Using the same technique, any FIFO of (63m+1)-words by 4n-bits can be configured, where m is the number of devices in a column and n is the number of devices in a row. Figure 7 and Figure 8 illustrate the timing diagrams for serial data entry and extraction for the FIFO shown in Figure 6. Figure 9 illustrates the final

positions of bits in an expanded 74F433 FIFO resulting from a 2032-bit serial bit train.

Interlocking Circuitry—Most conventional FIFO designs provide status signal analogous to IRF and ORE. However, when these devices are operated in arrays, variations in unit-to-unit operating speed require external gating to ensure that all devices have completed an operation. The 74F433 incorporates simple but effective 'master/slave' interlocking circuitry to eliminate the need for external gating.

In the 74F433 array of Figure 6, devices 1 and 5 are the row masters; the other devices are slaves to the master in their rows. No slave in a given row initializes its input register until it has received a LOW on its IES input from a row master or a slave of higher priority.

Similarly, the ORE outputs of slaves do not go HIGH until their inputs have gone HIGH. This interlocking scheme ensures that new input data may be accepted by the array when the IRF output of the final slave in that row goes HIGH and that output data for the array may be extracted when the ORE output of the final slave in the output row goes HIGH.

The row master is established by connecting its IES input to ground, while a slave receives its IES input from the IRF output of the next-higher priority device. When an array of 74F433 FIFOs is initialized with a HIGH on the MR inputs of all devices, the IRF outputs of all devices are HIGH. Thus, only the row master receives a LOW on the IES input during initialization.

Figure 10 is a conceptual logic diagram of the internal circuitry that determines master/slave operation. When MR and IES are LOW, the master latch is set. When TTS goes LOW, the initialization flip-flop is set. If the master latch is HIGH, the input register is immediately initialized and the initialization flip-flop reset. If the master latch is reset, the input register is not initialized until IES goes LOW. In array operation, activating TTS initiates a ripple input register initialization from the row master to the last slave.

A similar operation takes place for the output register. Either a TOS or TOP input initiates a load-from-stack operation and sets the ORE request flip-flop. If the master latch is set, the last output register flip-flop is set and the ORE line goes HIGH. If the master latch is reset, the ORE output is LOW until a Serial Output Enable ($\overline{OES}$) input is received.

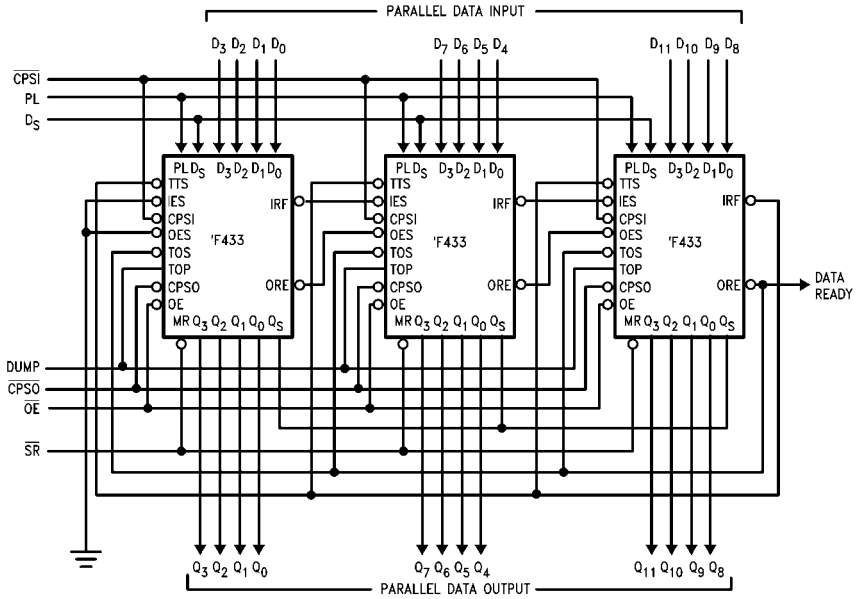


FIGURE 5. A Horizontal Expansion Scheme

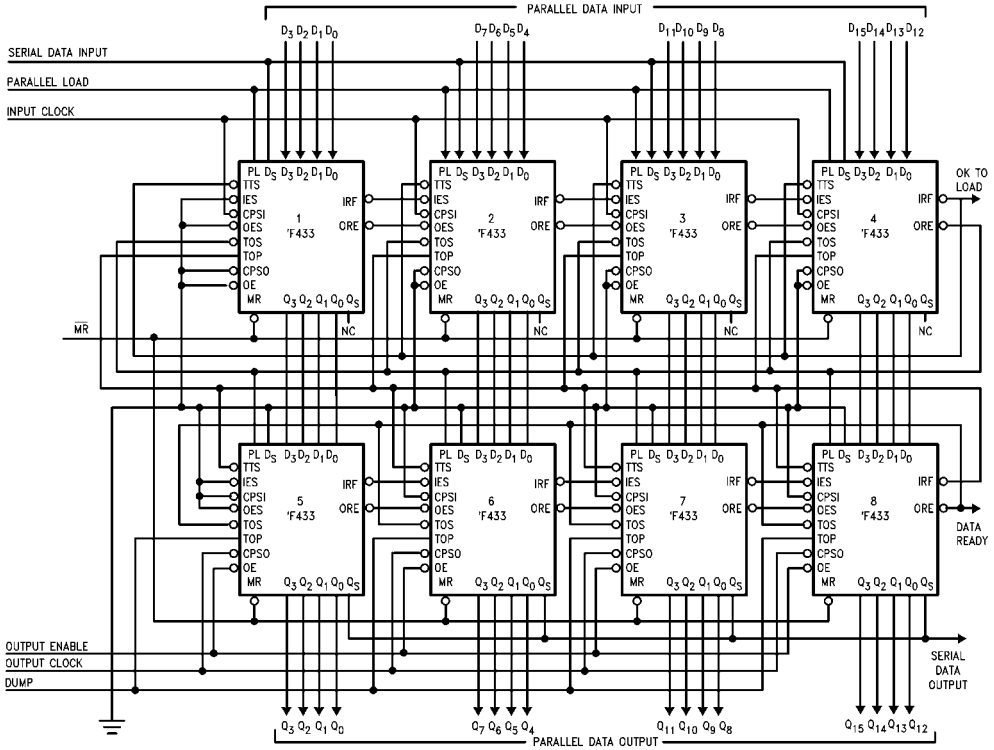


FIGURE 6. A 127 x 16 FIFO Array

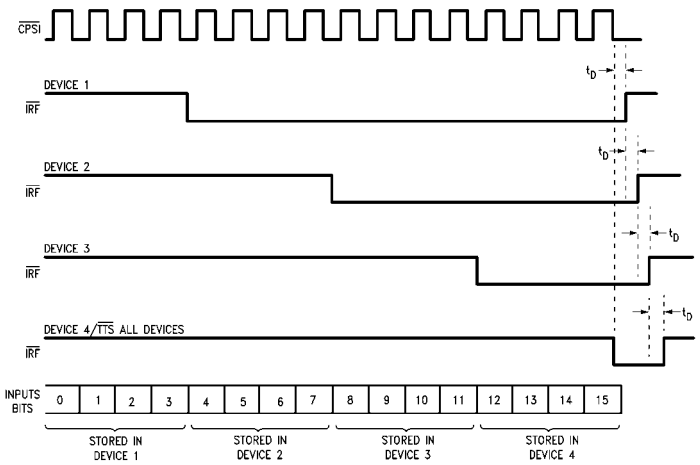


FIGURE 7. Serial Data Entry for Array of Figure

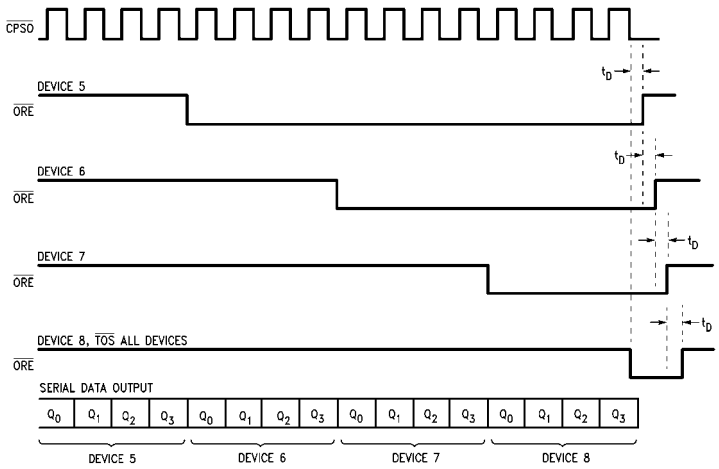


FIGURE 8. Serial Data Extraction for Array of Figure

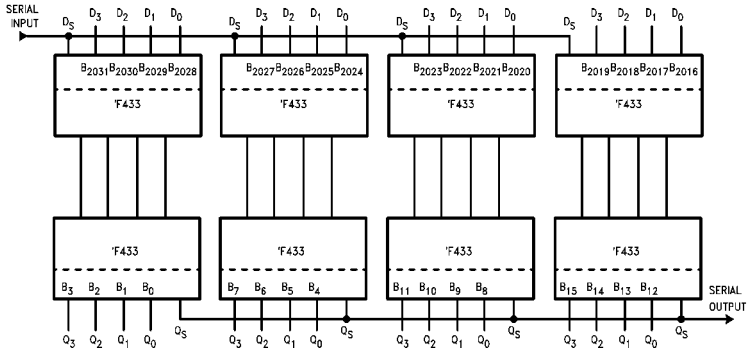


FIGURE 9. Final Position of a 2032-Bit Serial Input

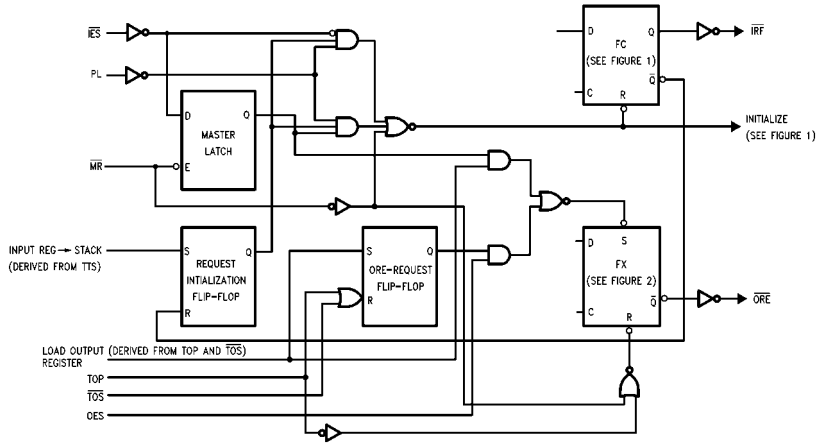


FIGURE 10. Conceptual Diagram, Interlocking Circuitry

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.5	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = 400 µA ($\overline{ORE}$, $\overline{IRF}$)
		10% V_{CC}	2.4					I_{OH} = 5.7 mA (Q_n, Q_s)
		5% V_{CC}	2.7					I_{OH} = 400 µA ($\overline{ORE}$, $\overline{IRF}$)
		5% V_{CC}	2.7					I_{OH} = 5.7 mA (Q_n, Q_s)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.50	V	Min	I_{OL} = 16 mA (Q_n, Q_s)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.4	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V (Q_n, Q_s)
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V (Q_n, Q_s)
I_{OS}	Output Short-Circuit Current		−20		−130	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			150	215	mA	Max	

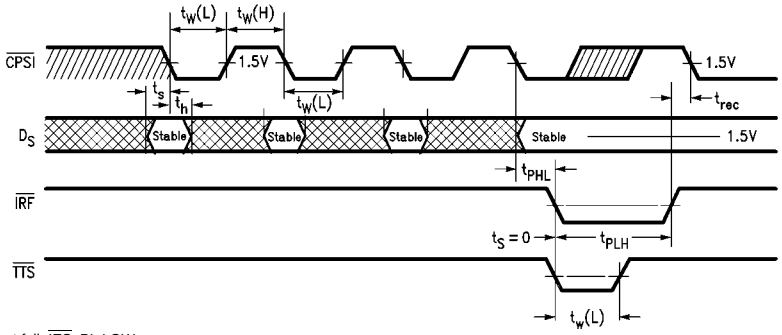
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units	Figure Number
		Min	Max	Min	Max		
t_{PHL}	Propagation Delay, Negative-Going CPSI to $\overline{IRF}$ Output	2.0	17.0	2.0	18.0	ns	Figure 11 Figure 12
t_{PLH}	Propagation Delay, Negative-Going $\overline{TTS}$ to $\overline{IRF}$	9.0	34.0	8.0	38.0		
t_{PLH}	Propagation Delay, Negative-Going	4.0	25.0	3.0	27.0	ns	Figure 13 Figure 14
t_{PHL}	$\overline{CPSO}$ to Q_S Output	5.0	20.0	5.0	21.0		
t_{PLH}	Propagation Delay, Positive-Going	8.0	35.0	7.0	38.0	ns	Figure 15
t_{PHL}	TOP to Q_0–Q_3 Outputs	7.0	30.0	7.0	32.0		
t_{PHL}	Propagation Delay, Negative-Going $\overline{CPSO}$ to $\overline{ORE}$	7.0	25.0	6.0	28.0	ns	Figure 13 Figure 14
t_{PHL}	Propagation Delay, Negative-Going TOP to $\overline{ORE}$	6.0	26.0	6.0	28.0	ns	Figure 15
t_{PLH}	Propagation Delay, Positive-Going TOP to $\overline{ORE}$	13.0	48.0	12.0	51.0		
t_{PLH}	Propagation Delay, Negative-Going $\overline{TOS}$ to Positive-Going $\overline{ORE}$	13.0	45.0	12.0	50.0	ns	Figure 13 Figure 14
t_{PHL}	Propagation Delay, Positive-Going PL to Negative-Going $\overline{IRF}$	4.0	22.0	4.0	23.0	ns	Figure 17 Figure 18
t_{PLH}	Propagation Delay, Negative-Going PL to Positive-Going $\overline{IRF}$	7.0	31.0	6.0	35.0		
t_{PLH}	Propagation Delay, Positive-Going $\overline{OES}$ to $\overline{ORE}$	9.0	38.0	8.0	44.0	ns	
t_{PLH}	Propagation Delay Positive-$\overline{IRF}$ Going $\overline{IES}$ to Positive-Going	5.0	25.0	5.0	27.0	ns	Figure 18
t_{PHL}	Propagation Delay MR to $\overline{ORE}$	7.0	28.0	7.0	31.0	ns	
t_{PLH}	Propagation Delay MR to $\overline{IRF}$	5.0	27.0	5.0	30.0	ns	
t_{PZH}	Enable Time	1.0	16.0	1.0	18.0	ns	
t_{PZL}	$\overline{OE}$ to Q_0–Q_3	1.0	14.0	1.0	16.0		
t_{PHZ}	Disable Time	1.0	10.0	1.0	12.0		
t_{PLZ}	$\overline{OE}$ to Q_0–Q_3	1.0	23.0	1.0	30.0		
t_{PZH}	Enable Time	1.0	10.0	1.0	12.0	ns	
t_{PZL}	Negative-Going $\overline{OES}$ to Q_S	1.0	14.0	1.0	15.0		
t_{PHZ}	Disable Time	1.0	10.0	1.0	12.0		
t_{PLZ}	Negative-Going $\overline{OES}$ to Q_S	1.0	14.0	1.0	16.0		
t_{PZH}	Enable Time	1.0	35.0	1.0	42.0	ns	
t_{PZL}	$\overline{TOS}$ to Q_S	1.0	35.0	1.0	39.0		
t_{DFT}	Fall-Through Time	0.2	0.9	0.2	1.0	ns	Figure 16
t_{AP}	Parallel Appearance Time $\overline{ORE}$ to Q_0–Q_3	–20.0	–2.0	–20.0	–2.0	ns	
t_{AS}	Serial Appearance Time $\overline{ORE}$ to Q_S	–20.0	5.0	–20.0	5.0		

AC Operating Requirements

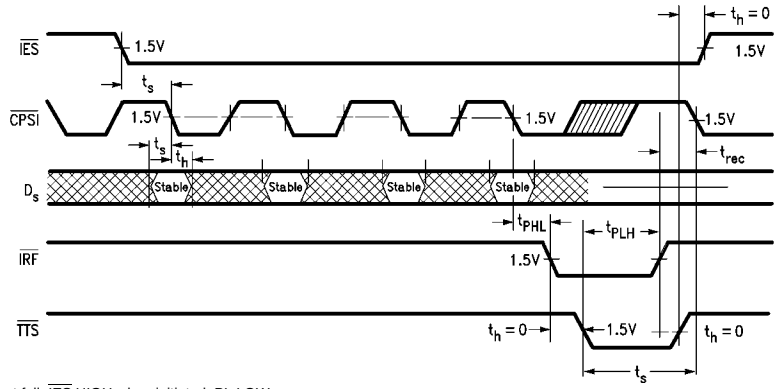
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units	Figure Number
		Min	Max	Min	Max		
$t_S(H)$	Setup Time, HIGH or LOW	7.0		7.0		ns	Figure 11 Figure 12
$t_S(L)$	D_S to Negative $\overline{CPSI}$	7.0		7.0			
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0			
$t_H(L)$	D_S to $\overline{CPSI}$	2.0		2.0			
$t_S(L)$	Setup Time, LOW $\overline{TTS}$ to $\overline{IRF}$, Serial or Parallel Mode	0.0		0.0		ns	Figure 11 Figure 12 Figure 17 Figure 18
$t_S(L)$	Setup Time, LOW Negative-Going $\overline{ORE}$ to Negative-Going $\overline{TOS}$	0.0		0.0		ns	Figure 13 Figure 14
$t_S(L)$	Setup Time, LOW Negative-Going $\overline{IES}$ to $\overline{CPSI}$	8.0		9.0		ns	Figure 12
$t_S(L)$	Setup Time, LOW Negative-Going $\overline{TTS}$ to $\overline{CPSI}$	30.0		33.0			
$t_S(H)$	Setup Time, HIGH or LOW	0.0		0.0		ns	
$t_S(L)$	Parallel Inputs to PL	0.0		0.0			
$t_H(H)$	Hold Time, HIGH or LOW	4.0		4.0			
$t_H(L)$	Parallel Inputs to PL	4.0		4.0			
$t_W(H)$	$\overline{CPSI}$ Pulse Width	10.0		11.0		ns	Figure 11 Figure 12
$t_W(L)$	HIGH or LOW	5.0		6.0			
$t_W(H)$	PL Pulse Width, HIGH	7.0		9.0		ns	Figure 17 Figure 18
$t_W(L)$	$\overline{TTS}$ Pulse Width, LOW Serial or Parallel Mode	7.0		9.0		ns	Figure 11 Figure 12 Figure 13 Figure 14
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	7.0		9.0		ns	Figure 16
$t_W(H)$	TOP Pulse Width	14.0		16.0		ns	Figure 15
$t_W(L)$	HIGH or LOW	7.0		7.0			
$t_W(H)$	$\overline{CPSO}$ Pulse Width	14.0		16.0		ns	Figure 13 Figure 14
$t_W(L)$	HIGH or LOW	7.0		7.0			
t_{REC}	Recovery Time $\overline{MR}$ to Any Input	8.0		15.0		ns	Figure 16

Timing Waveforms



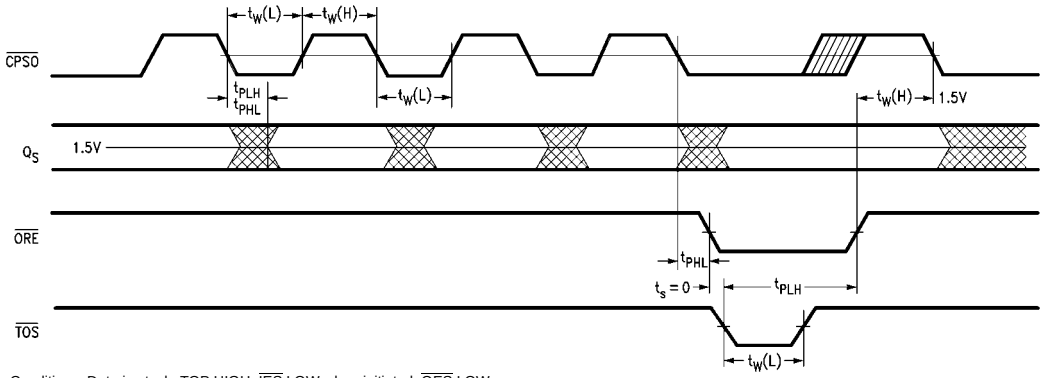
Conditions: Stack not full, $\overline{IES}$, PL LOW

FIGURE 11. Serial Input, Unexpanded or Master Operation



Conditions: Stack not full, $\overline{IES}$ HIGH when initiated, PL LOW

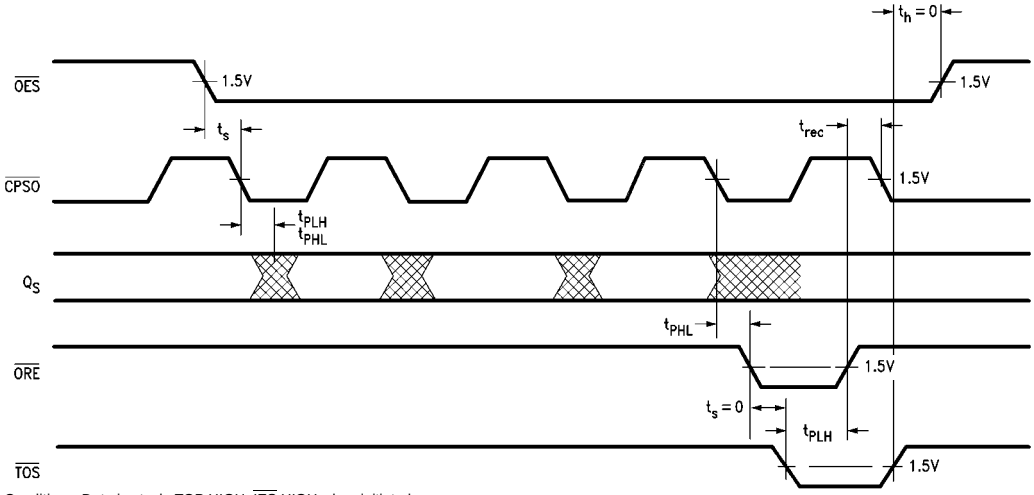
FIGURE 12. Serial Input, Expanded Slave Operation



Conditions: Data in stack, TOP HIGH, $\overline{IES}$ LOW when initiated, $\overline{OES}$ LOW

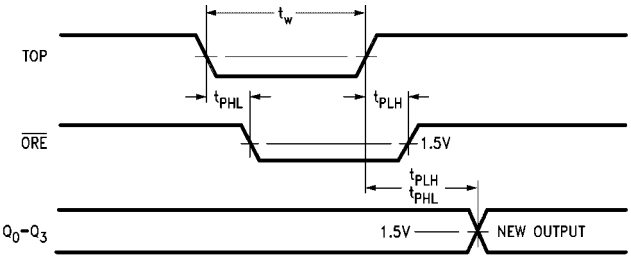
FIGURE 13. Serial Output, Unexpanded or Master Operation

Timing Waveforms (Continued)



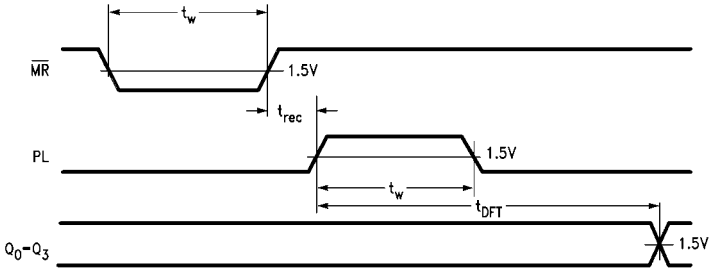
Conditions: Data in stack, TOP HIGH, $\overline{IES}$ HIGH when initiated

FIGURE 14. Serial Output, Slave Operation



Conditions: $\overline{IES}$ LOW when initiated, $\overline{OE}$, $\overline{CPSO}$ LOW; data available in stack

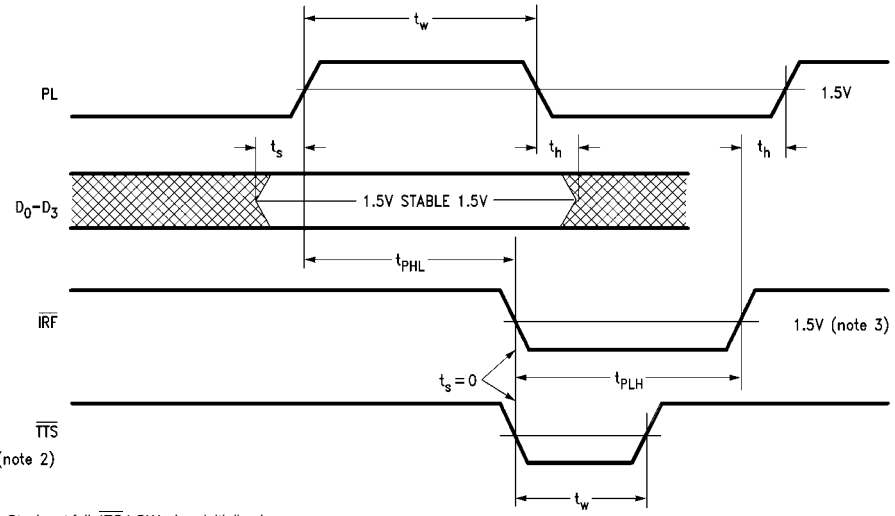
FIGURE 15. Parallel Output, 4-Bit Word or Master in Parallel Expansion



Conditions: $\overline{TTS}$ connected to $\overline{IRF}$, $\overline{TOS}$ connected to $\overline{ORE}$, $\overline{IES}$, $\overline{OES}$, $\overline{OE}$, $\overline{CPSO}$ LOW, TOP HIGH

FIGURE 16. Fall Through Time

Timing Waveforms (Continued)

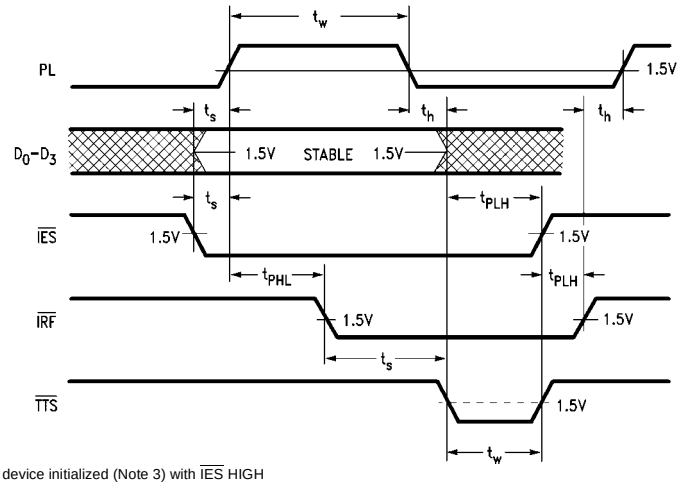


Conditions: Stack not full, $\overline{IES}$ LOW when initialized

NOTE A: $\overline{TTS}$ normally connected to $\overline{IRF}$.

NOTE B: If stack is full, $\overline{IRF}$ will stay LOW.

FIGURE 17. Parallel Load Mode, 4-Bit Word (Unexpanded) or Master in Parallel Expansion

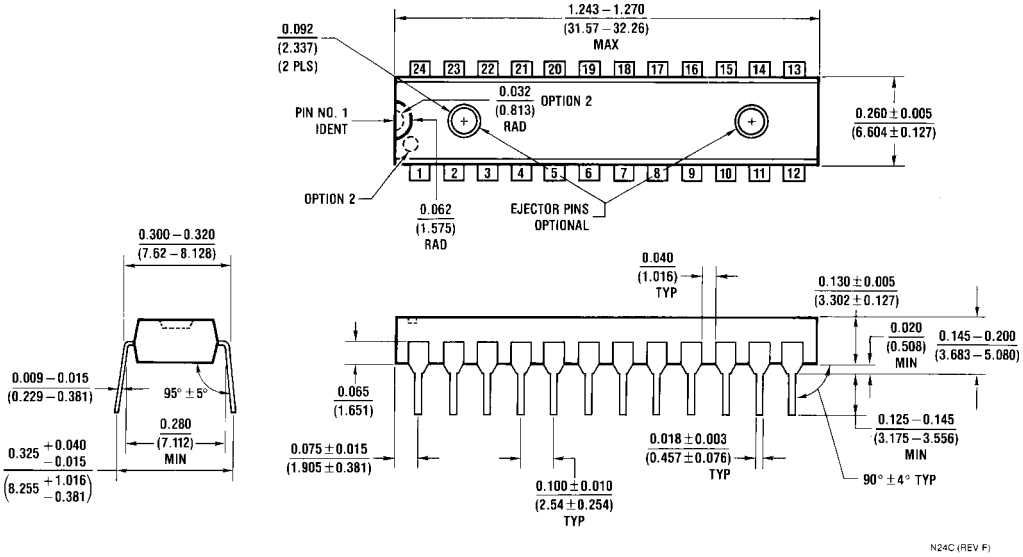


Conditions: Stack not full, device initialized (Note 3) with $\overline{IES}$ HIGH

Note 3: Initialization requires a master reset to occur after power has been applied.

FIGURE 18. Parallel Load, Slave Mode

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F51
Dual 2-Wide 2-Input; 2-Wide 3-Input AND-OR-Invert Gate

General Description

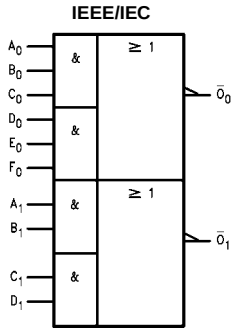
This device contains two independent logic units, one performing a 2-2 AND-OR-INVERT and the other performing a 3-3 AND-OR-INVERT function.

Ordering Code:

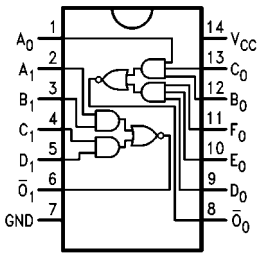
Order Number	Package Number	Package Description
74F51SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F51SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F51PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n, C_n, D_n, E_n, F_n	Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_n$	Outputs	50/33.3	–1 mA/20 mA

Function Table for 3-Input Gates

Inputs						Output
A_0	B_0	C_0	D_0	E_0	F_0	$\overline{O}_0$
H	H	H	X	X	X	L
X	X	X	H	H	H	L
All other combinations						H

Function Table for 2-Input Gates

Inputs				Output
A_1	B_1	C_1	D_1	$\overline{O}_1$
H	H	X	X	L
X	X	H	H	L
All other combinations				H

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

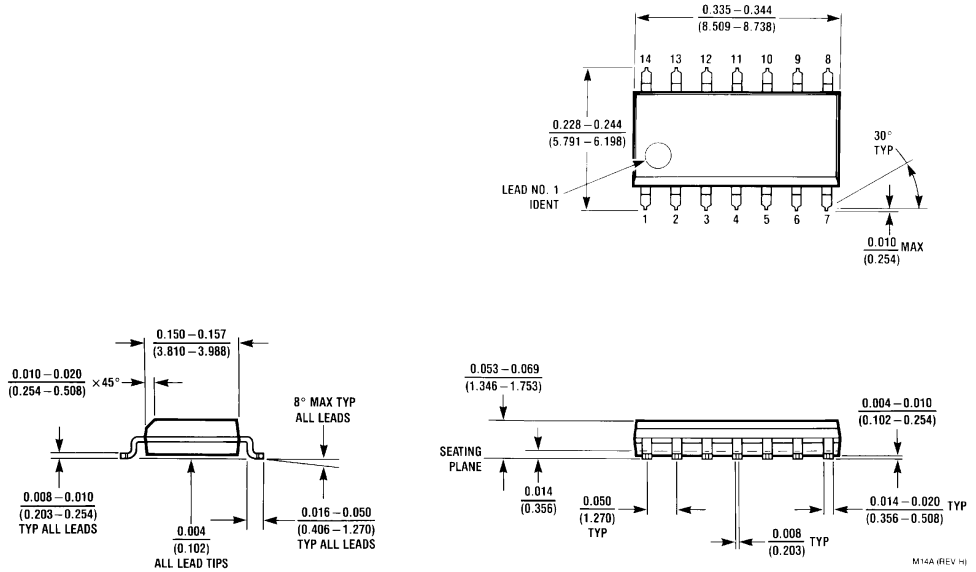
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			1.9	3.0	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			5.3	8.5	mA	Max	V_O = LOW

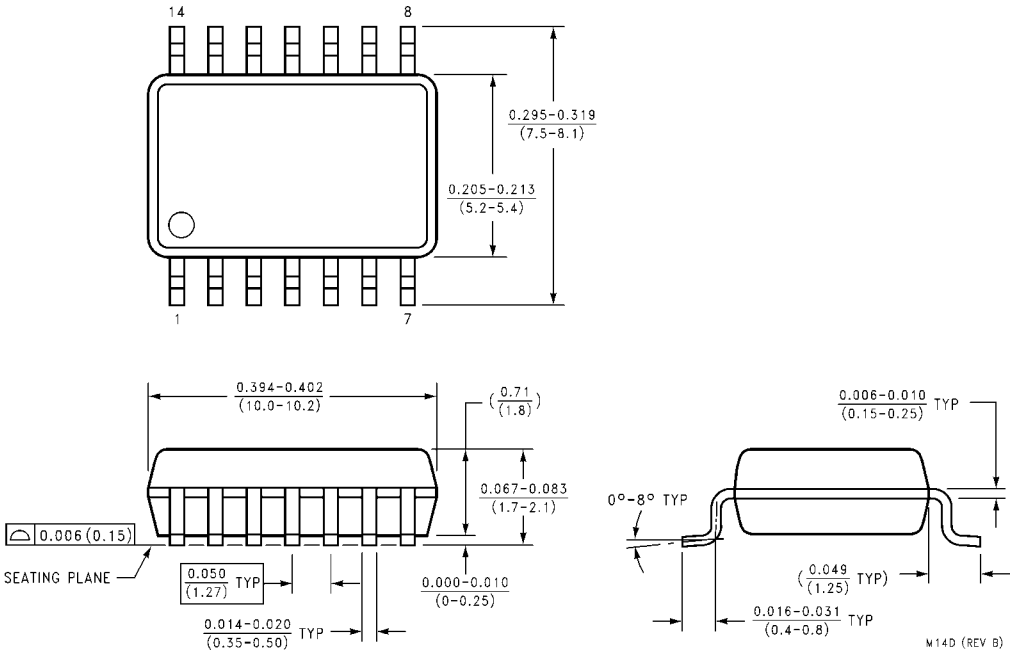
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.0	3.7	6.0	1.5	6.5	ns
t_{PHL}	A_n, B_n, C_n, D_n, E_n, F_n to $\overline{O}_n$	1.0	2.6	4.0	1.0	4.5	

Physical Dimensions inches (millimeters) unless otherwise noted

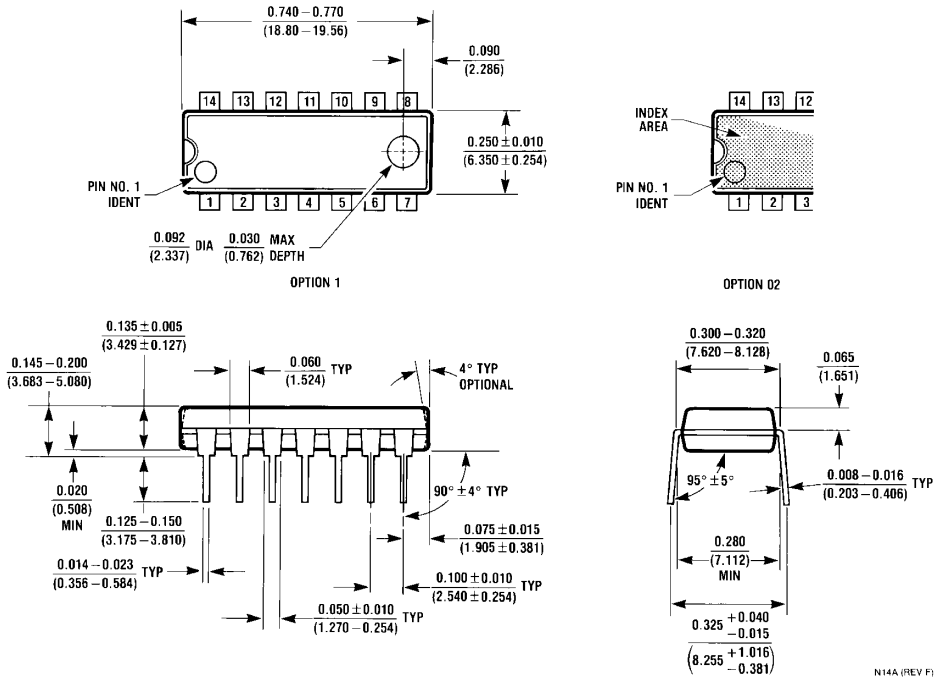


14-Lead Small Outline Integrated Circuit (SOC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F521
8-Bit Identity Comparator

General Description

The 74F521 is an expandable 8-bit comparator. It compares two words of up to eight bits each and provides a LOW output when the two words match bit for bit. The expansion input $\overline{I}_{A=B}$ also serves as an active LOW enable input.

Features

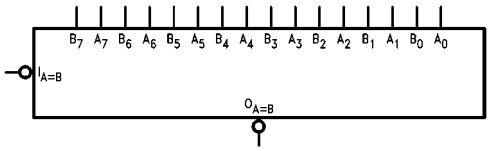
- Compares two 8-bit words in 6.5 ns typ
- Expandable to any word length
- 20-pin package

Ordering Code:

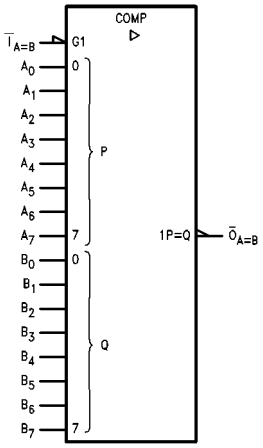
Order Number	Package Number	Package Description
74F521SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F521SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F521MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F521PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

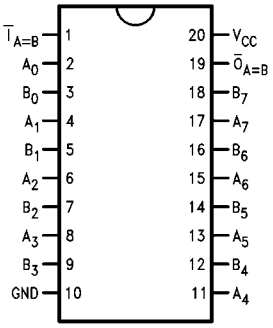
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Word A Inputs	1.0/1.0	20 μA/–0.6 mA
B_0–B_7	Word B Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{I}_{A=B}$	Expansion or Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_{A=B}$	Identity Output (Active LOW)	50/33.3	–1 mA/20 mA

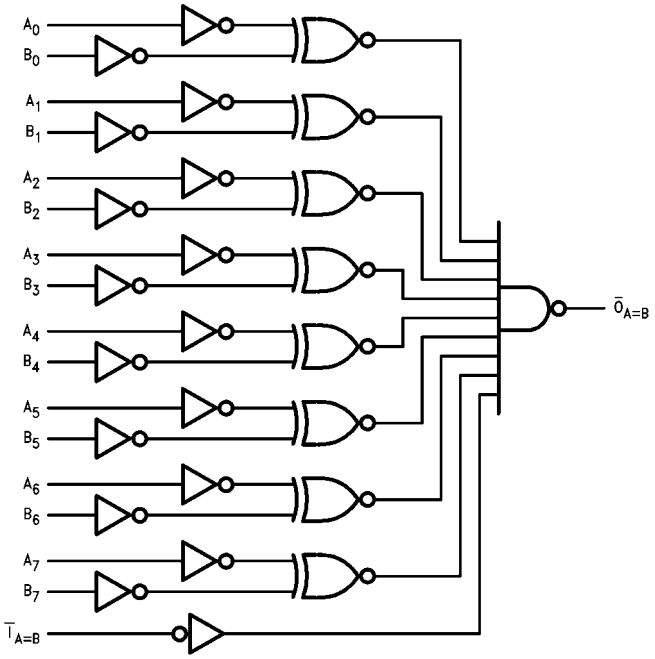
Truth Table

Inputs		Output
$\overline{I}_{A=B}$	A, B	$\overline{O}_{A=B}$
L	A = B (Note 1)	L
L	A ≠ B	H
H	A = B (Note 1)	H
H	A ≠ B	H

H = HIGH Voltage Level
L = LOW Voltage Level

Note 1: $A_0 = B_0$, $A_1 = B_1$, $A_2 = B_2$, etc.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

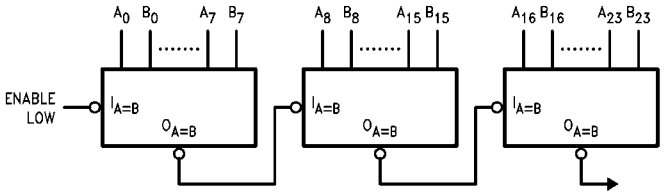
Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			21	32	mA	Max	V_O = HIGH

AC Electrical Characteristics

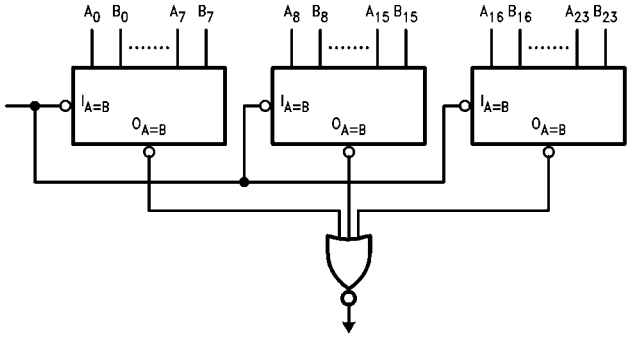
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	7.0	10.0	3.0	14.0	3.0	11.0	ns
t_{PHL}	A_n or B_n to $\overline{O}_{A=B}$	4.5	7.0	10.0	4.0	15.0	4.0	11.0	
t_{PLH}	Propagation Delay	3.0	5.0	6.5	3.0	8.5	3.0	7.5	ns
t_{PHL}	$\overline{I}_{A=B}$ to $\overline{O}_{A=B}$	3.5	6.5	9.0	3.5	13.5	3.5	10.0	

Applications

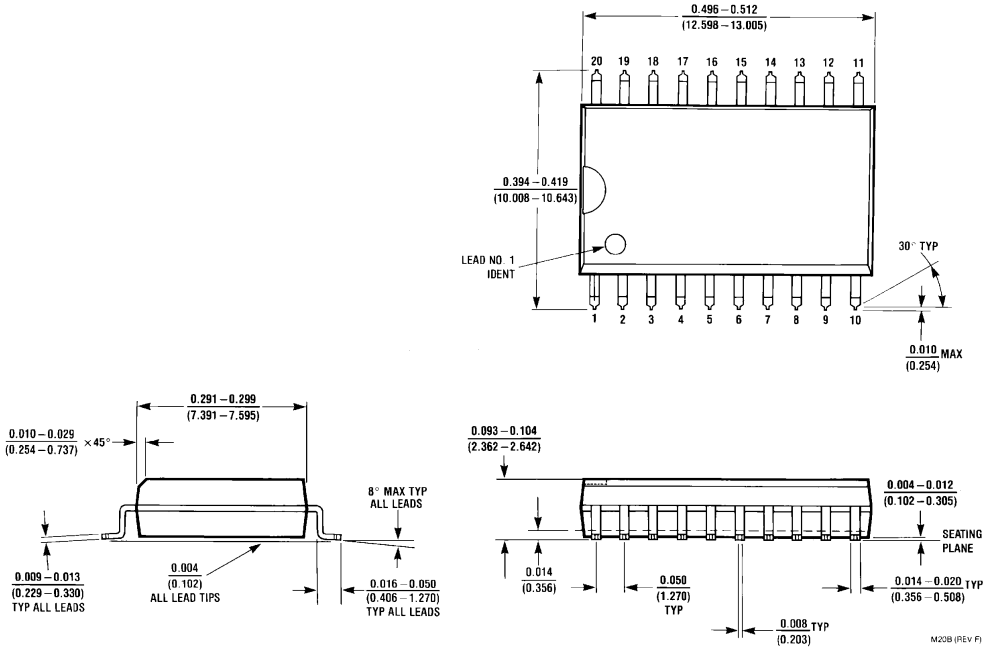
Ripple Expansion



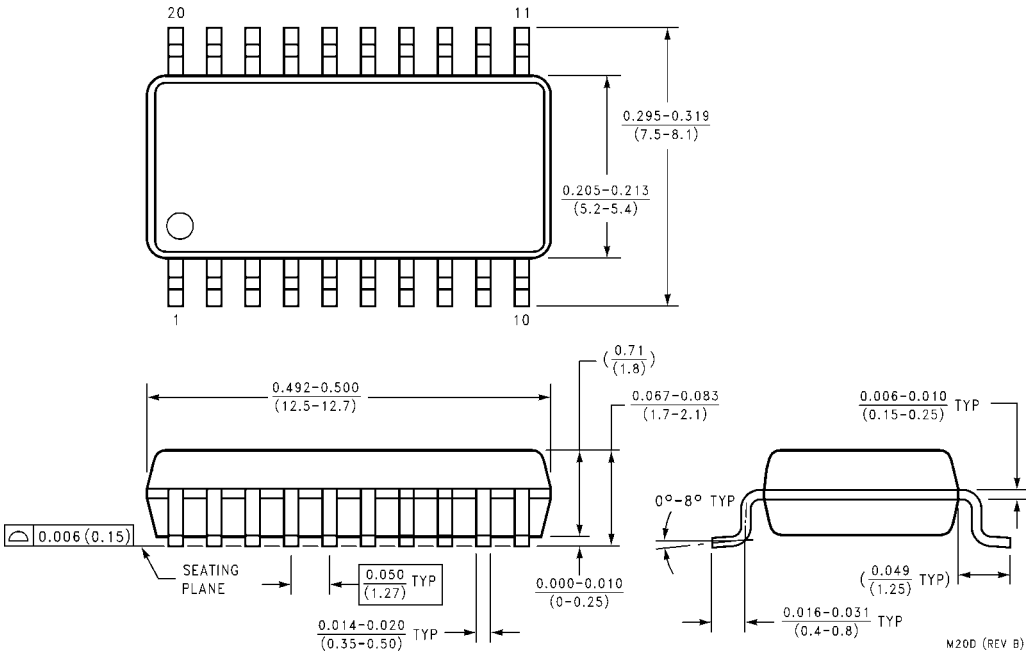
Parallel Expansion



Physical Dimensions inches (millimeters) unless otherwise noted

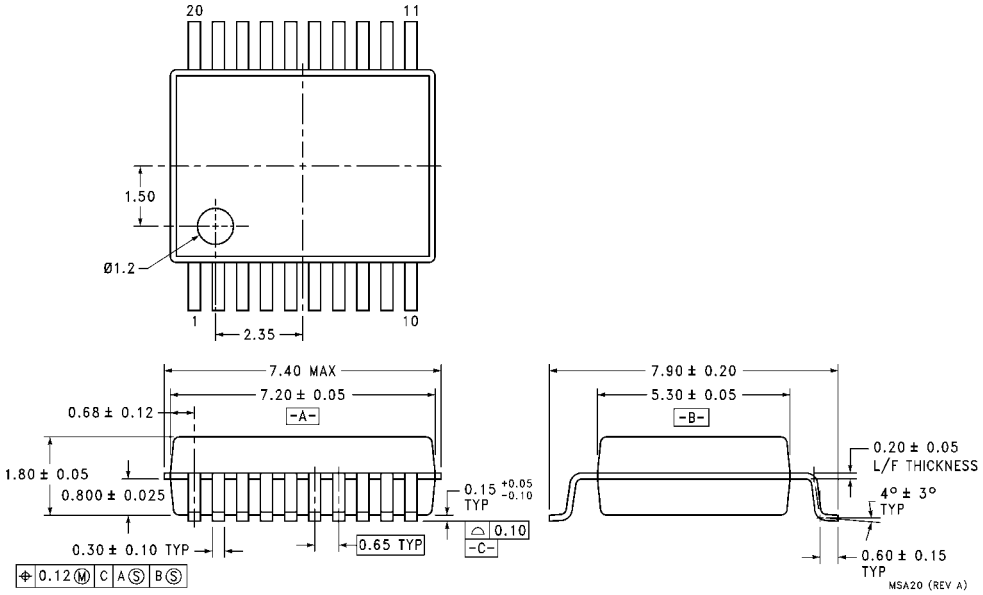


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



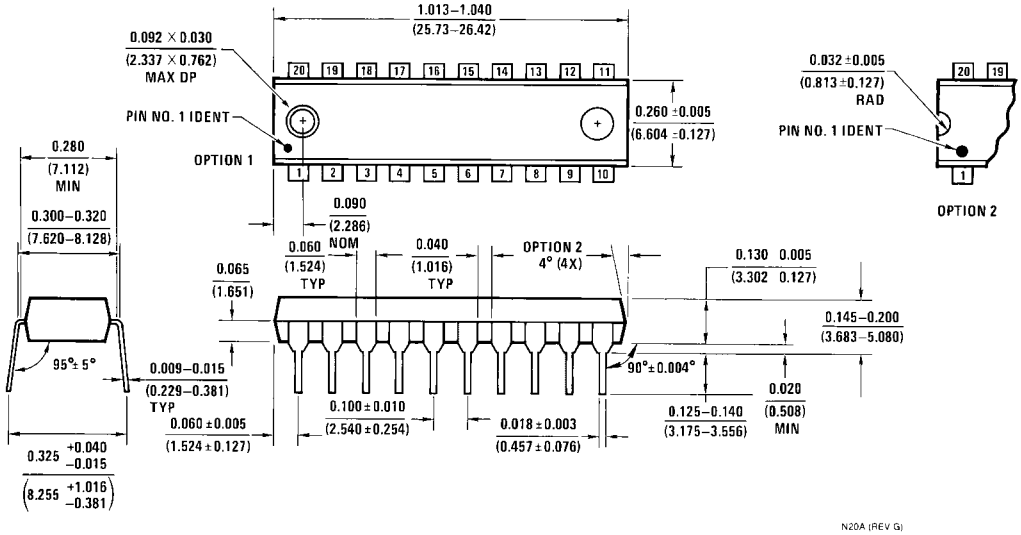
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F524
8-Bit Registered Comparator

General Description

The 74F524 is an 8-bit bidirectional register with parallel input and output plus serial input and output progressing from LSB to MSB. All data inputs, serial and parallel, are loaded by the rising edge of the input clock. The device functions are controlled by two control lines (S_0, S_1) to execute shift, load, hold and read out.

An 8-bit comparator examines the data stored in the registers and on the data bus. Three true-HIGH, open-collector outputs representing "register equal to bus", "register greater than bus" and "register less than bus" are provided. These outputs can be disabled to the OFF state by the use of Status Enable ($\overline{SE}$). A mode control has also been provided to allow twos complement as well as magnitude compare. Linking inputs are provided for expansion to longer words.

Features

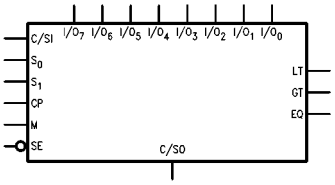
- 8-Bit bidirectional register with bus-oriented input-output
- Independent serial input-output to register
- Register bus comparator with "equal to", "greater than" and "less than" outputs
- Cascadable in groups of eight bits
- Open-collector comparator outputs for AND-wired expansion
- Twos complement or magnitude compare

Ordering Code:

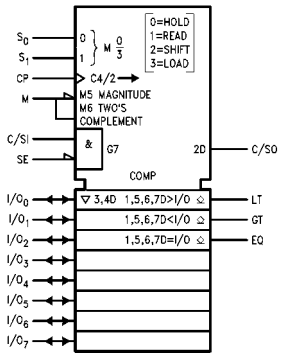
Order Number	Package Number	Package Description
74F524SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F524PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

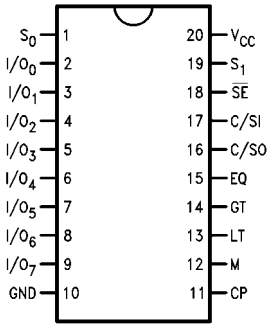
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0, S_1	Mode Select Inputs	1.0/1.0	20 μA/–0.6 mA
C/SI	Status Priority or Serial Data Input	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{SE}$	Status Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
M	Compare Mode Select Input	1.0/1.0	20 μA/–0.6 mA
I/O_0–I/O_7	Parallel Data Inputs or	3.5/1.083	70 μA/–0.65 mA
	3-STATE Parallel Data Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)
C/SO	Status Priority or Serial Data Output	50/33.3	–1 mA/20 mA
LT	Register Less Than Bus Output	OC (Note 1) /33.3	(Note 1) /20 mA
EQ	Register Equal Bus Output	OC(Note 1) /33.3	(Note 1) /20 mA
GT	Register Greater Than Bus Output	OC(Note 1) /33.3	(Note 1) /20 mA

Note 1: OC = Open Collector

Number Representation Select Table

M	Operation
L	Magnitude Compare
H	Twos Complement Compare

Select Truth Table

S_0	S_1	Operation
L	L	Hold—Retains Data in Shift Register
L	H	Read—Read Contents in Register onto Data Bus,
		Data Remains in Register Unaffected by Clock
H	L	Shift—Allows Serial Shifting on Next Rising Clock Edge
H	H	Load—Load Data on Bus into Register

Status Truth Table

(Hold Mode)

Inputs			Outputs			
$\overline{SE}$	C/SI	Data Comparison	EQ	GT	LT	C/SO
H	H	X	H	H	H	1
L	L	O_A–O_H > I/O_0–I/O_7	L	H	H	L
X	L	O_A–O_H = I/O_0–I/O_7	H	H	H	L
H	L	O_A–O_H < I/O_0–I/O_7	L	H	H	L
H	H	O_A–O_H > I/O_0–I/O_7	L	H	L	L
H	H	O_A–O_H = I/O_0–I/O_7	H	L	L	H
L	H	O_A–O_H < I/O_0–I/O_7	L	L	H	L

1 = HIGH if data are equal, otherwise LOW
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Description

The 74F524 contains eight D-type flip-flops connected as a shift register with provision for either parallel or serial loading. Parallel data may be read from or loaded into the registers via the data bus I/O_0–I/O_7. Serial data is entered from the C/SI input and may be shifted into the register and out through the C/SO output. Both parallel and serial data entry occur on the rising edge of the input clock (CP). The operation of the shift register is controlled by two signals S_0 and S_1 according to the Select Truth Table. The 3-STATE parallel output buffers are enabled only in the Read mode.

One port of an 8-bit comparator is attached to the data bus while the other port is tied to the outputs of the internal register. Three active-OFF, open-collector outputs indicate whether the contents held in the shift register are “greater than”, (GT), “less than” (LT), or “equal to” (EQ) the data on the input bus. A HIGH signal on the Status Enable ($\overline{SE}$) input disables these outputs to the OFF state. A mode control input (M) allows selection between a straightforward magnitude compare or a comparison between twos complement numbers.

For “greater than” or “less than” detection, the C/SI input must be held HIGH, as indicated in the Status Truth Table. The internal logic is arranged such that a LOW signal on the C/SI input disables the “greater than” and “less than” outputs. The C/SO output will be forced HIGH if the “equal to” status condition exists, otherwise C/SO will be held LOW. These facilities enable the 74F524 to be cascaded for word length greater than eight bits.

Word length expansion (in groups of eight bits) can be achieved by connecting the C/SO output of the more significant byte to the C/SI input of the next less significant byte and also to its own $\overline{SE}$ input (see Figure 1). The C/SI input of the most significant device is held HIGH while the $\overline{SE}$ input of the least significant device is held LOW. The corresponding status outputs are AND-wired together. In the case of twos complement number compare, only the Mode input to the most significant device should be HIGH. The Mode inputs to all other cascaded devices are held LOW.

Suppose that an inequality condition is detected in the most significant device. Assuming that the byte stored in the register is greater than the byte on the data bus, the EQ and LT outputs will be pulled LOW and the GT output will float HIGH. Also the C/SO output of the most significant device will be forced LOW, disabling the subsequent devices but enabling its own status outputs. The correct status condition is thus indicated. The same applies if the registered byte is less than the data byte, only in this case the EQ and GT outputs go LOW and LT output floats HIGH.

If an equality condition is detected in the most significant device, its C/SO output is forced HIGH. This enables the next less significant device and also disables its own status outputs. In this way, the status output priority is handed down to the next less significant device which now effectively becomes the most significant byte. The worst case propagation delay for a compare operation involving “n” cascaded 74F524s will be when an equality condition is detected in all but the least significant byte. In this case, the status priority has to ripple all the way down the chain before the correct status output is established. Typically, this will take $35 + 6(n-2)$ ns.

Function Diagram

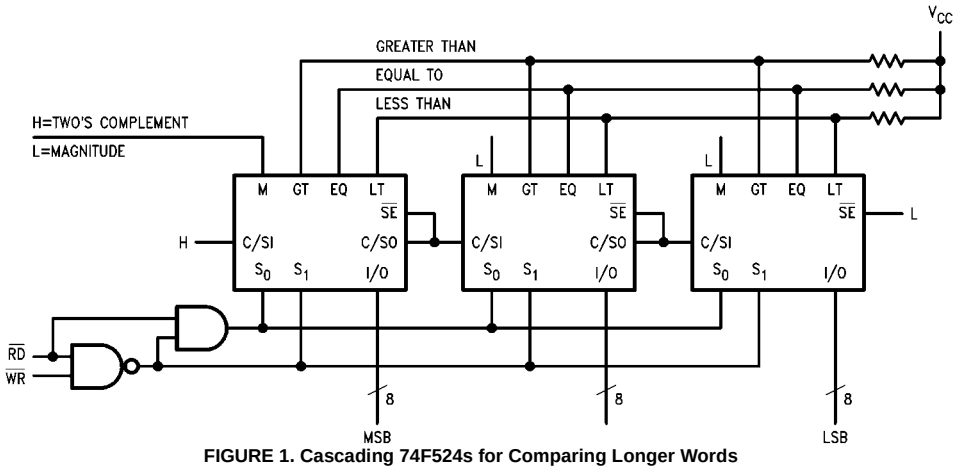
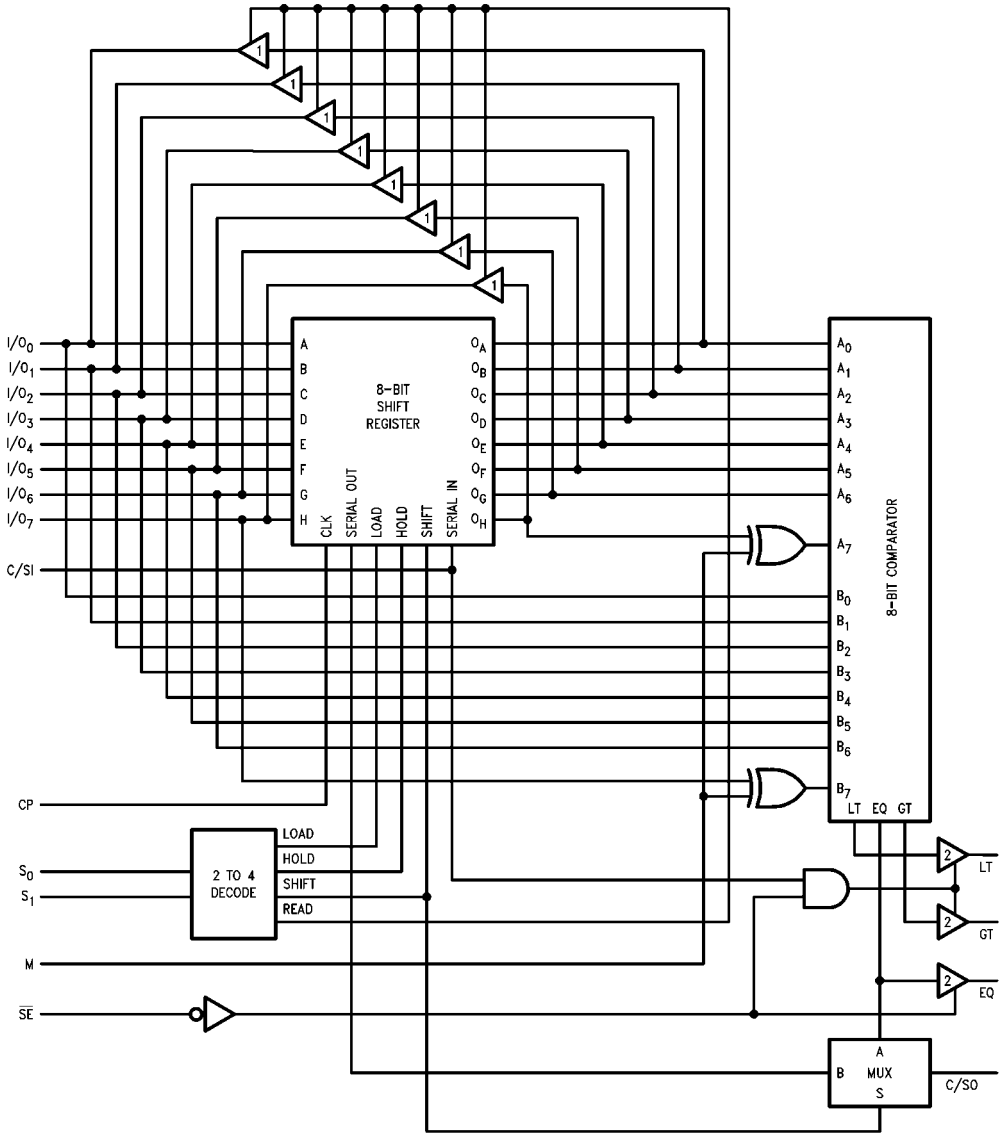


FIGURE 1. Cascading 74F524s for Comparing Longer Words

Block Diagram



Notes:

1. 3-STATE Output
2. Open-Collector Output

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA (I/O_n)
	Voltage	10% V_{CC}			0.5			I_{OL} = 24 mA (LT, GT, EQ, C/SO)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC} (I/O_n, C/SO)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	$V_{I/O}$ = 2.7V
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	$V_{I/O}$ = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{OHC}	Open Collector, Output OFF Leakage Test				250	µA	Min	V_{OUT} = V_{CC}
I_{CCH}	Power Supply Current			128	180	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			128	180	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			128	180	mA	Max	V_O = HIGH Z

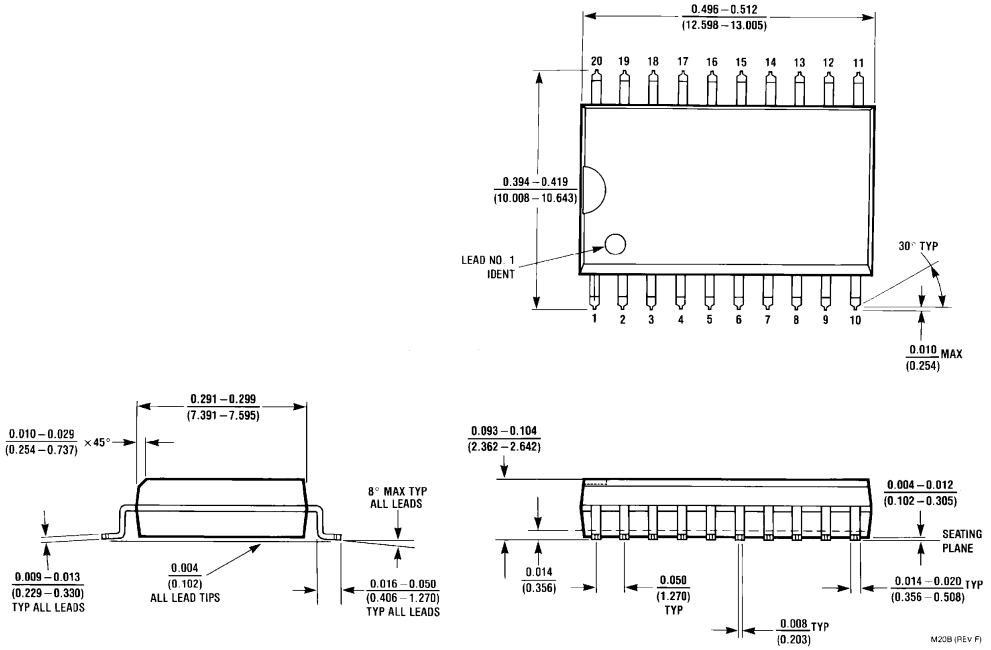
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Shift Frequency	50	75		50		MHz
t_{PLH}	Propagation Delay	9.0	16.5	20.0	9.0	21.0	ns
t_{PHL}	I/O_n to EQ	5.0	9.5	12.0	5.0	13.0	
t_{PLH}	Propagation Delay	8.5	14.1	19.0	8.5	20.0	ns
t_{PHL}	I/O_n to GT	6.5	13.0	16.5	6.5	17.5	
t_{PLH}	Propagation Delay	7.0	15.5	20.0	7.0	21.0	
t_{PHL}	I/O_n to LT	4.5	10.0	14.0	4.5	15.0	
t_{PLH}	Propagation Delay	8.0	15.2	19.5	8.0	20.5	ns
t_{PHL}	I/O_n to C/SO	6.0	12.5	16.0	6.0	17.0	
t_{PLH}	Propagation Delay	10.0	20.0	25.0	10.0	26.0	ns
t_{PHL}	CP to EQ	4.0	8.5	16.5	4.0	17.5	
t_{PLH}	Propagation Delay	10.0	16.5	21.0	10.0	22.0	ns
t_{PHL}	CP to GT	8.5	17.0	22.0	8.5	23.0	
t_{PLH}	Propagation Delay	9.0	20.0	25.0	9.0	26.0	
t_{PHL}	CP to LT	5.5	13.5	17.0	5.5	18.0	
t_{PLH}	Propagation Delay CP to C/SO (Load)	8.5	16.5	21.0	8.5	22.0	ns
t_{PLH}	Propagation Delay	5.0	10.0	13.0	5.0	14.0	
t_{PHL}	CP to C/SO (Serial Shift)	4.5	9.0	11.5	4.5	12.5	
t_{PLH}	Propagation Delay	9.0	15.0	19.0	9.0	20.0	ns
t_{PHL}	C/SI to GT	3.0	6.5	8.5	3.0	9.5	
t_{PLH}	Propagation Delay	8.0	15.5	20.0	8.0	21.0	
t_{PHL}	C/SI to LT	3.5	6.5	8.5	3.5	9.5	
t_{PLH}	Propagation Delay	6.5	11.5	14.5	6.5	15.5	ns
t_{PHL}	S_0, S_1 to C/SO	5.5	14.0	18.0	5.5	19.0	
t_{PLH}	Propagation Delay	3.5	8.0	10.5	3.5	11.5	
t_{PHL}	$\overline{SE}$ to EQ	2.5	6.0	8.0	2.5	9.0	
t_{PLH}	Propagation Delay	6.5	12.5	16.0	6.5	17.0	ns
t_{PHL}	$\overline{SE}$ to GT	3.5	6.0	8.0	3.5	9.0	
t_{PLH}	Propagation Delay	5.0	10.5	13.5	5.0	14.5	
t_{PHL}	$\overline{SE}$ to LT	3.5	6.0	8.0	3.5	9.0	
t_{PLH}	Propagation Delay	4.0	8.5	11.0	4.0	12.0	ns
t_{PHL}	C/SI to C/SO	4.0	8.5	11.0	4.0	12.0	
t_{PLH}	Propagation Delay	8.0	15.0	19.5	8.0	20.5	ns
t_{PHL}	M to GT	6.0	12.0	17.5	6.0	18.5	
t_{PLH}	Propagation Delay	8.0	17.0	22.0	8.0	23.0	
t_{PHL}	M to LT	4.5	9.5	12.0	4.5	13.0	
t_{PLH}	Propagation Delay	15.0	25.0	33.0	15.0	35.0	ns
t_{PHL}	S_0, S_1 to EQ	9.0	15.0	19.0	9.0	20.0	
t_{PLH}	Propagation Delay	10.5	18.0	23.0	10.5	24.0	
t_{PHL}	S_0, S_1 to GT	10.5	18.0	23.0	10.5	24.0	
t_{PLH}	Propagation Delay	13.0	22.0	28.0	13.0	30.0	
t_{PHL}	S_0, S_1 to LT	12.0	19.0	24.0	12.0	25.0	
t_{PZH}	Output Enable Time	4.5	10.0	13.0	4.5	14.0	ns
t_{PZL}	S_0, S_1 to I/O_n	5.5	11.0	15.0	5.5	16.0	
t_{PHZ}	Output Disable Time	3.5	8.0	12.0	3.5	13.0	
t_{PLZ}	S_0, S_1 to I/O_n	4.5	9.6	12.5	4.5	13.5	

AC Operating Requirements

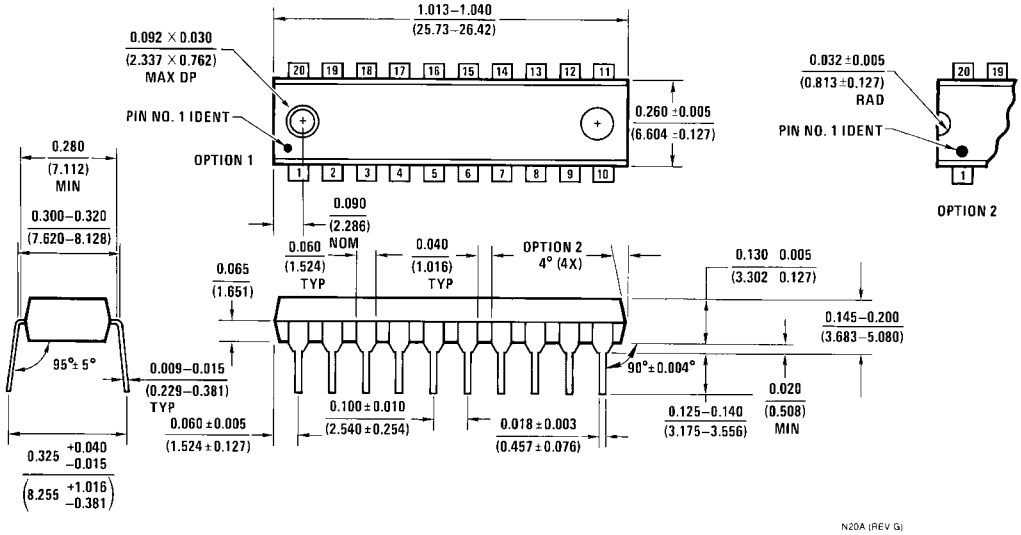
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	6.0		6.0		ns
$t_S(L)$	I/O_n to CP	6.0		6.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	I/O_n to CP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	10.0		10.0		ns
$t_S(L)$	S_0 or S_1 to CP	10.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	S_0 or S_1 to CP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	7.0		7.0		ns
$t_S(L)$	C/SI to CP	7.0		7.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	C/SI to CP	0		0		
$t_W(H)$	Clock Pulse Width, HIGH	5.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

National Semiconductor

August 1995

74F525
Programmable Counter

General Description

The 'F525 is a multi-function 28-pin device. It consists of a 16-bit count-down counter, logic to control the counter, logic to control the state of the outputs and a PLA to decode the particular function selected by the user. The list of high-speed timing applications include:

Features

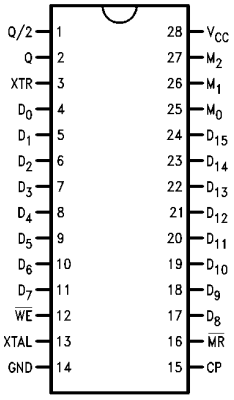
- Baud rate generator
- Digitally programmed monostable
- Variable system frequency generator
- Digital filter variable sampling rate
- 16-bit data path
- External trigger
- Extremely accurate one shot w/pulse widths from 50 ns to 3.27 ms @CP = 40 MHz

Commercial	Package Number	Package Description
74F525QC (Note 1)	V28A	28-Lead Molded Plastic Leaded Chip Carrier
74F525SC (Note 1)	M28B	28-Lead (0.300″ Wide) Molded Small Outline, JEDEC
74F525PC	N28B	28-Lead (0.600″ Wide) Molded Dual-In-Line Package

Note 1: Devices also available in 13″ reel. Use suffix = SCX and QCX.

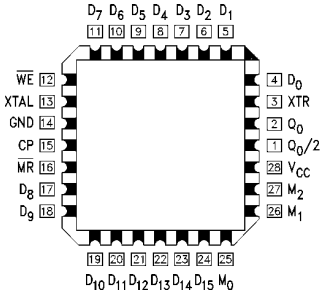
Connection Diagrams

Pin Assignment DIP and SOIC



TL/F/9547–2

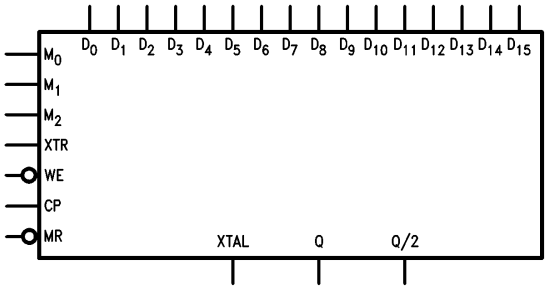
Pin Assignment for PCC



TL/F/9547–3

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Logic Symbol



TL/F/9547–1

Unit Loading/Fan Out

Pin Names	Description	74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
Q	Ouput (Primarily indicates when the counter has reached zero)	50/33.3	−1 mA/20 mA
Q/2	Output (Divides Q by 2)	50/33.3	−1 mA/20 mA
M_0–M_2	Status Inputs	1.0/1.0	20 μA/−0.6 mA
$\overline{MR}$	Master Reset	1.0/1.0	20 μA/−0.6 mA
CP	Clock Pulse	1.0/2.0	20 μA/−1.2 mA
D_0–D_{15}	Data Inputs	1.0/1.0	20 μA/−0.6 mA
$\overline{WE}$	Write Enable Input	1.0/1.0	20 μA/−0.6 mA
XTR	External Trigger Input	1.0/2.0	20 μA/−1.2 mA
XTAL	Crystal Output	1.0/1.0	20 μA/−0.6 mA

Functional Description

The multi-function aspect of the device consists of eight different modes of operation. An explanation of the operation of the device in each of the modes follows. However, there is one operation that is independent of the selected mode: the loading of data. Data is latched into a set of data latches when $\overline{WE}$ is brought from a LOW to a HIGH state. The latches are transparent when $\overline{WE}$ is held LOW.

Operation Notes:

1. Device should be reset before operation.
2. The XTR input acts as a select line for the clock.
3. With XTR low, the clock goes into the counter.
4. With XTR high, the clock loads the counter.
5. In mode 4 and 5, during counting, the counter cannot be reloaded. XTR high freezes the count.
6. Mode 7 is the only auto-reload mode, all other modes require and XTR pulse to begin.
7. Loading 0 into the latches idles the device.

MODE 0: Interval Timer with Level Output

While XTR is HIGH, the data in the data latches is loaded into the counter upon the next positive edge of CP. The negative edge of XTR enables the count-down to begin with the next positive edge of CP. When the count reaches zero, Q, normally LOW, is brought HIGH and Q/2 toggles state. Taking XTR HIGH at any time enables the data in the data latches to be loaded into the counter on the rising edge of CP and clears Q. See *Figure 1*.

MODE 1: Interval Timer with Inverted Level Output

The operation is exactly the same as in Mode 0 except that Q is normally HIGH and goes LOW when the count reaches zero. Q/2 toggles on the negative-edge of Q. See *Figure 1*.

MODE 2: Interval Timer with Pulse Output

While XTR is HIGH, the data in the data latches is loaded into the counter upon the next positive edge of CP. The negative edge of XTR enables the count-down to begin with the next positive edge of CP. When the count reaches zero, Q, normally LOW, is brought HIGH for a single period of CP. Q/2 toggles state on the positive edge of Q. Taking XTR HIGH at any time causes the data in the data latches to be loaded into the counter on the rising edge of CP and clears Q. See *Figure 2*.

MODE 3: Interval Timer with Inverted Pulse Output

The operation is exactly the same as in Mode 2 except that Q is normally HIGH and goes LOW for a single period of CP. Q/2 toggles on the negative edge of Q. See *Figure 2*.

Functional Description (Continued)

Function Table

M_2	M_1	M_0	Function
0	0	0	Mode 0
0	0	1	Mode 1
0	1	0	Mode 2
0	1	1	Mode 3
1	0	0	Mode 4
1	0	1	Mode 5
1	1	0	Mode 6
1	1	1	Mode 7

MODE 4: Interval Timer, Pulse Output with Count Hold

While XTR is HIGH, the data in the data latches is loaded into the counter upon the next positive edge of CP. The negative edge of XTR enables the count-down to begin with the next positive edge of CP. When the count reaches zero, Q, normally low, is brought HIGH for a single period of CP. Q/2 toggles state on the positive edge of Q. Taking XTR HIGH before the counters reach zero, stops the count-down from the point where it was held. Data cannot be reloaded into the counter until a count of zero is reached. See *Figure 3*.

MODE 5: Interval Timer, Inverted Pulse Output with Count Hold

The operation is exactly the same as Mode 4 except that Q is normally HIGH and goes LOW for a single period of CP. Q/2 toggles on the negative-edge of Q. See *Figure 3*.

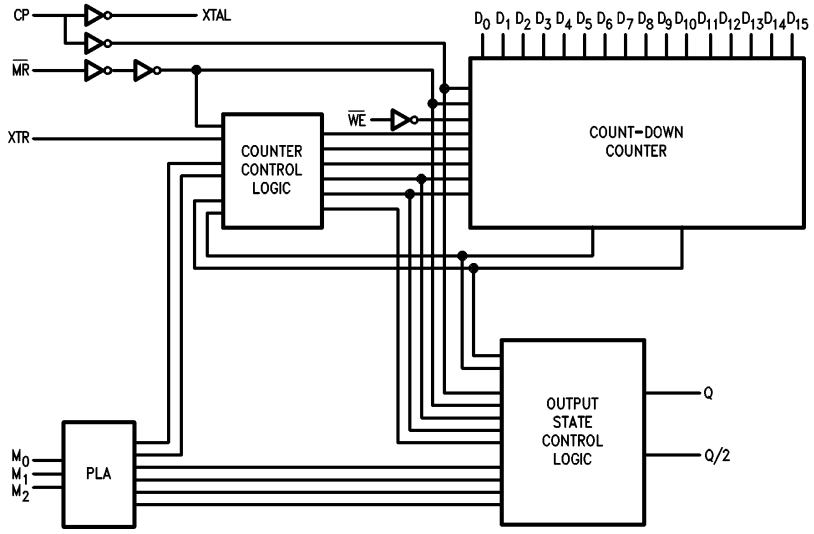
MODE 6: Retriggerable Synchronous One-Shot

When XTR is HIGH, the data in the data latches is loaded into the counter upon the positive edge of CP. The negative edge of XTR enables the count-down to begin with the next positive edge of CP, wehre Q, normally LOW, is then brought HIGH and the counter is decremented when the count reaches zero, Q is brought LOW, and Q/2 is toggled. Bringing XTR HIGH during the count-down will allow the data in the data latches to be loaded into the counter with the next positive edge of CP, but will not affect Q. See *Figure 4*. NOTE that the pulse width of Q will be N-1 clock cycles, where N is the number loaded into the counter. N = 1 should not be used as this may cause unpredictable results.

MODE 7: Frequency Generator

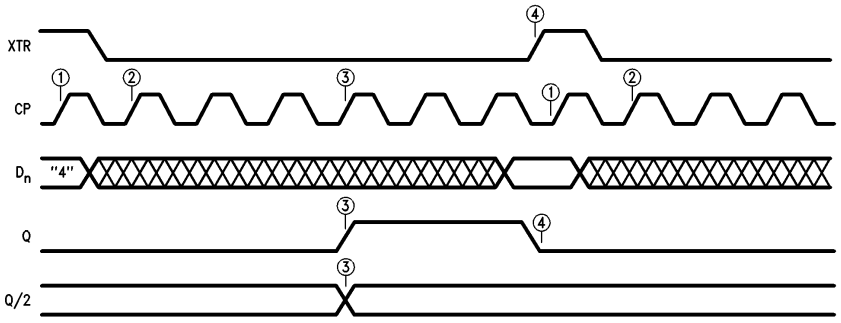
When XTR is HIGH, the data in the data latches is loaded into the counter upon the positive edge of CP. The negative edge of XTR enables the count-down to begin with the next positive edge of CP. When the count reaches zero, Q, normally LOW, is brought HIGH for a single period of CP and Q/2 is toggled. The same clock edge that brings Q HIGH, also loads the data in the data latches into the counter. The counter will start to count on the next positive edge of CP. This mode will run continuously after an initial XTR until stopped by MR. Taking XTR HIGH at any time causes the data in the data latches to be loaded into the counter and Q output to be cleared with the next positive edge of CP. See *Figure 5*.

Block Diagram



TL/F/9547–4

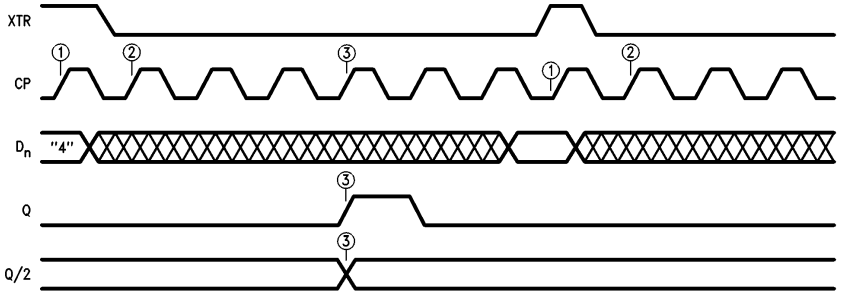
Timing Diagrams



TL/F/9547–5

①With XTR HIGH, the rising edge of CP loads data from the latches to the counter.
②With XTR LOW, the rising edge of CP begins count-down cycle.
③When the count reaches zero, Q goes HIGH, and Q/2 toggles state.
④The next occurrence of XTR clears Q.

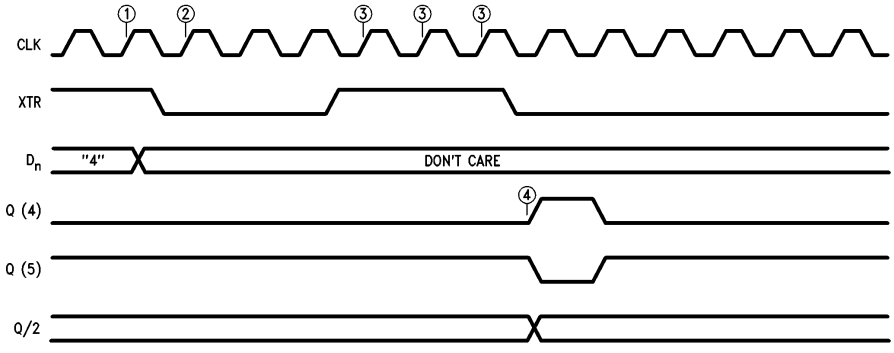
FIGURE 1. MODE 0 and MODE 1 (Inverse Output of Mode 0)
$\overline{M}_n$ = 000, 001



TL/F/9547–6

①With XTR HIGH, the rising edge of CP loads data from the latches to the counter.
②With XTR LOW, the rising edge of CP begins the count-down cycle.
③When the count reaches zero, Q goes HIGH for one period of CP, and Q/2 toggles state.

FIGURE 2. MODE 2 and MODE 3 (Inverse Output of Mode 2)
$\overline{M}_n$ = 010, 011

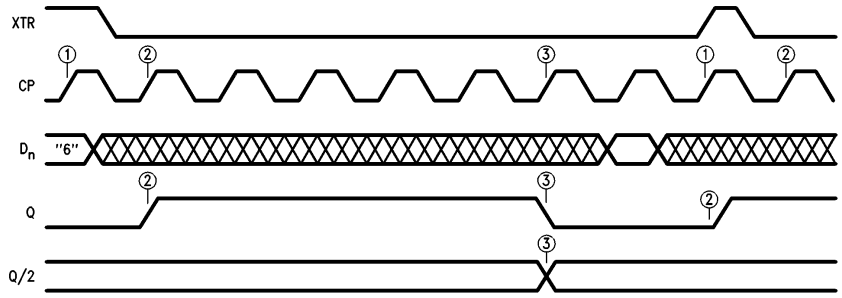


TL/F/9547–7

FIGURE 3. MODE 4 and MODE 5
$\overline{M}_n$ = 100, 101

①With XTR HIGH, the rising edge of CP loads data from the latches into the counter.
②With XTR LOW, the rising edge of CP begins the count-down.
③With XTR HIGH, during count-down, the rising edge of CP does nothing.
④When the count reaches zero, Q goes HIGH for one clock cycle and Q/2 toggles state.
Note: Once the count reaches zero, the counter can be reloaded with XTR HIGH.

Timing Diagrams (Continued)



TL/F/9547–8

FIGURE 4. MODE 6
$\overline{M}_n$ = 110

①With XTR HIGH, the rising edge of CP loads data from the latches to the counter.

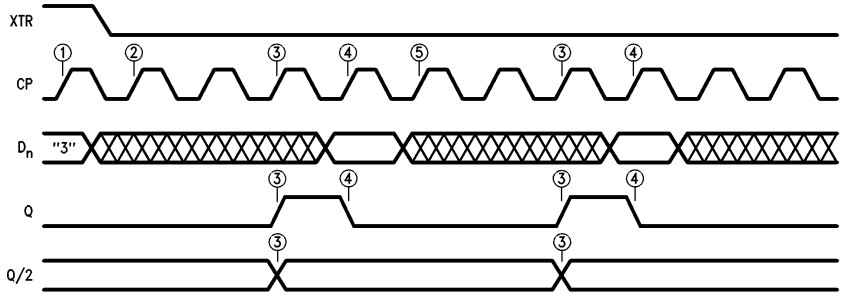
②With XTR LOW, the rising edge of CP begins the count, and Q goes HIGH.

③When the count reaches zero, Q goes LOW, and Q/2 toggles state. Bringing XTR HIGH before count reaches zero will reload the counter, but not affect Q.

Notes:

Loading N = 0 halts counter; loading N = 1 will result in undefined operation.

Pulse width = (2/CP) * (N − 1)



TL/F/9547–9

FIGURE 5. MODE 7
$\overline{M}_n$ = 111

①With XTR HIGH, the rising edge of CP, loads data from the latches to the counter.

②On the falling edge of XTR, the rising edge of CP begins count-down.

③When count reaches zero, Q goes HIGH for one period of CP, and Q/2 toggles on the Q rising edge.

④On the rising edge of CP on which Q goes LOW, the counters are reloaded.

⑤Count-down begins again.

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE® Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	0°C to +70°C
Supply Voltage	
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		74F			Units	V_{CC}	Conditions
			Min	Typ	Max			
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	74F 10% V_{CC} 74F 5% V_{CC}	2.5 2.7			V	Min	I_{OH} = −1 mA I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	74F 10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current	74F			5.0	μA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test	74F			7.0	μA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current	74F			50	μA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	74F	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current	74F			3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6 −1.2	mA	Max	V_{IN} = 0.5V (D0–D15) V_{IN} = 0.5V (CP, XTR)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			106	160	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			106	160	mA	Max	V_O = LOW

AC Electrical Characteristics

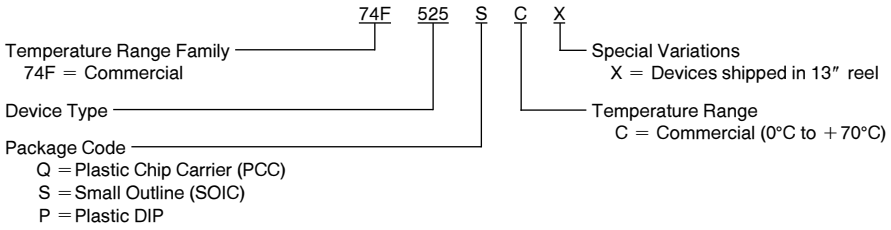
Symbol	Parameter	74F $T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			74F T_A, V_{CC} = Com, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	50	60		40		MHz
t_{PLH} t_{PHL}	Propagation Delay CP to Q	9.0 8.0	16.0 12.0	20.5 15.5	8.0 7.0	22.5 17.5	ns
t_{PLH} t_{PHL}	Propagation Delay CP to Q/2	9.0 10.0	15.5 15.5	20.0 20.0	8.0 9.0	22.0 22.0	ns
t_{PLH} t_{PHL}	Propagation Delay XTR to Q	8.5 6.0	12.0 10.5	15.5 13.5	7.5 5.0	17.5 15.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{MR}$ to Q	11.5 9.0	16.5 12.5	21.0 16.0	10.5 8.0	23.0 18.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{MR}$to Q/2	8.0 7.0	14.0 10.5	17.5 13.5	7.0 6.0	19.5 15.0	ns
t_{PLH} t_{PHL}	Propagation Delay M_n to Q	10.0 10.5	15.0 17.0	19.0 21.5	9.0 9.5	21.0 23.5	ns

AC Operating Requirements

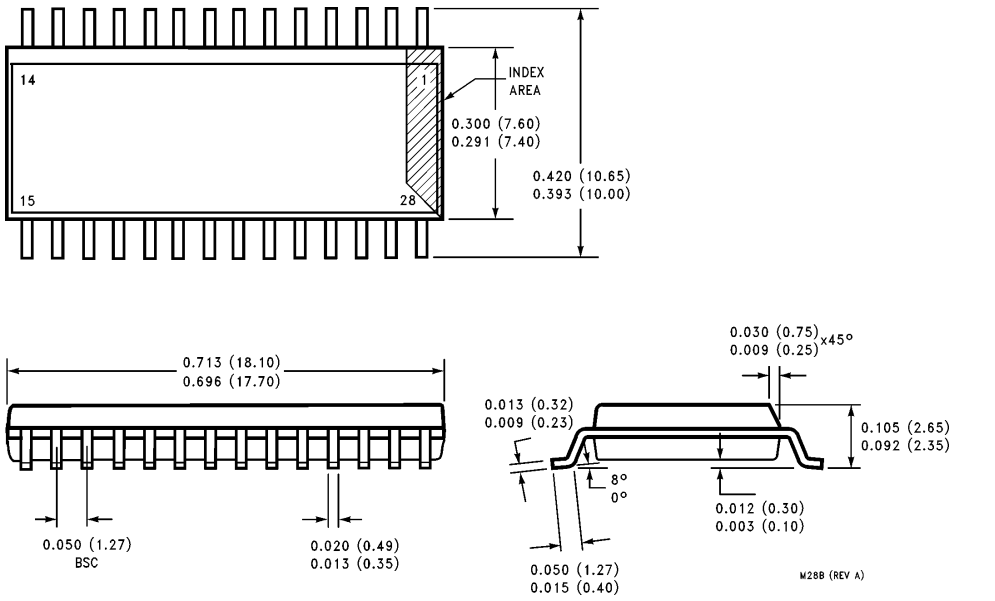
Symbol	Parameter	74F $T_A = +25°C$, $V_{CC} = +5.0V$		74F T_A, V_{CC} = Com		Units
		Min	Max	Min	Max	
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW D_n to $\overline{WE}$	2.0 4.0		2.5 4.5		ns
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW D_n to $\overline{WE}$	0 2.0		0 2.5		ns
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW D_n to CP	9.0 10.5		10.0 12.0		ns
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW D_n to CP	0 0		0 0		ns
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW XTR to CP	7.0 8.0		8.0 9.0		ns
$t_h(H)$	Hold Time, HIGH or LOW XTR to CP	0		0		ns
$t_s(H)$ $t_s(L)$	Setup Time, HIGH or LOW Mode to CP	33.5 33.5		35.5 35.5		ns
$t_w(H)$	XTR Pulse Width, HIGH	11.5		13.0		ns
$t_w(L)$	$\overline{MR}$ Pulse Width, LOW	7.0		8.0		ns
$t_w(L)$	$\overline{WE}$ Pulse Width, LOW	4.5		5.0		ns
$t_w(H)$ $t_w(L)$	CP Pulse Width HIGH or LOW	3.5 9.5		4.0 10.5		ns
t_{rec}	Recovery Time $\overline{MR}$ to CP	5.0		6.0		ns
t_{rec}	Recovery Time Mode to CP	30.0		32.0		ns

Ordering Information

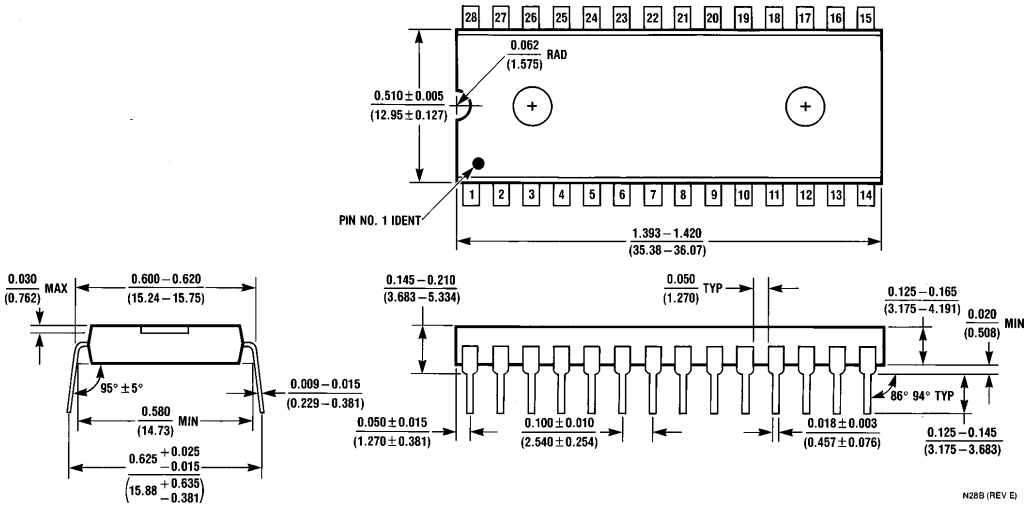
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)

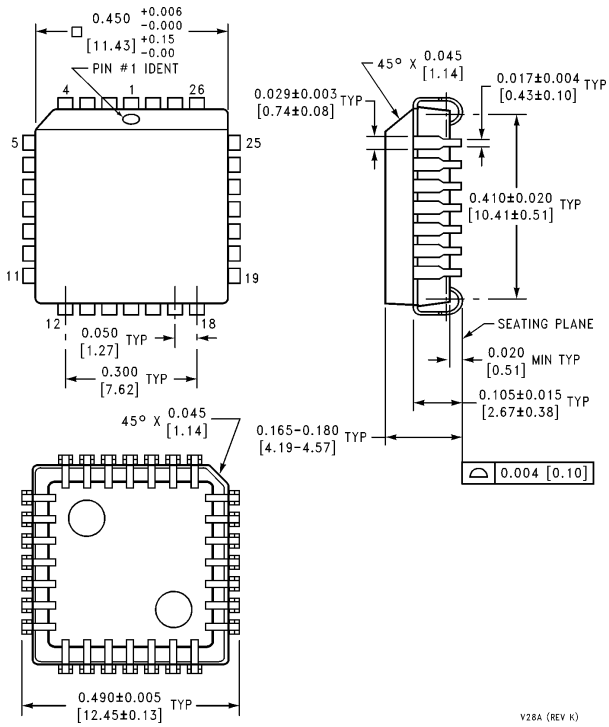


28-Lead (0.300″ Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M28B



28-Lead (0.600″ Wide) Molded Dual-In-Line Package, (P)
NS Package Number N28B

Physical Dimensions inches (millimeters) (Continued)



28-Lead Molded Plastic Leaded Chip Carrier (Q)
NS Package Number V28A

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F533
Octal Transparent Latch with 3-STATE Outputs

General Description

The 74F533 consists of eight latches with 3-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state. The 74F533 is the same as the 74F373, except that the outputs are inverted.

Features

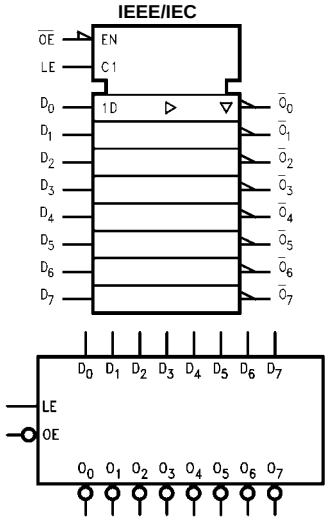
- Eight latches in a single package
- 3-STATE outputs for bus interfacing
- Inverted version of the 74F373

Ordering Code:

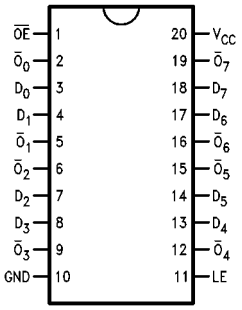
Order Number	Package Number	Package Description
74F533SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F533SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F533PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
LE	Latch Enable Input (Active HIGH)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_0$–$\overline{O}_7$	Complementary 3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Function Table

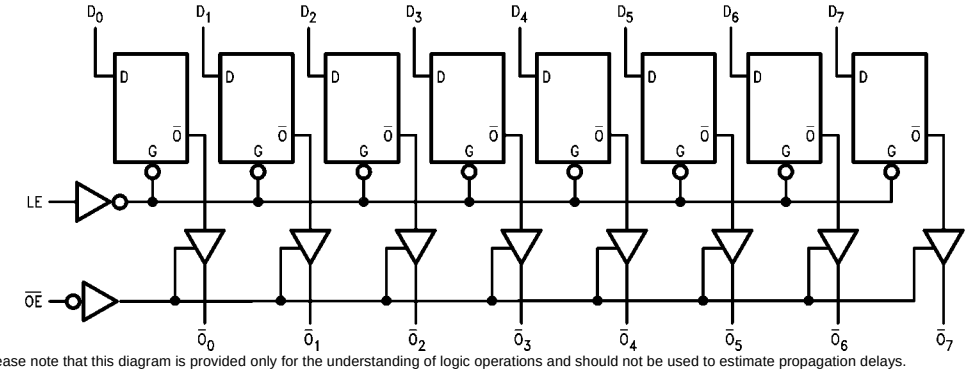
Inputs			Output
LE	$\overline{OE}$	D	$\overline{O}$
H	L	H	L
H	L	L	H
L	L	X	$\overline{O}_0$
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Description

The 74F533 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			41	61	mA	Max	V_O = HIGH Z

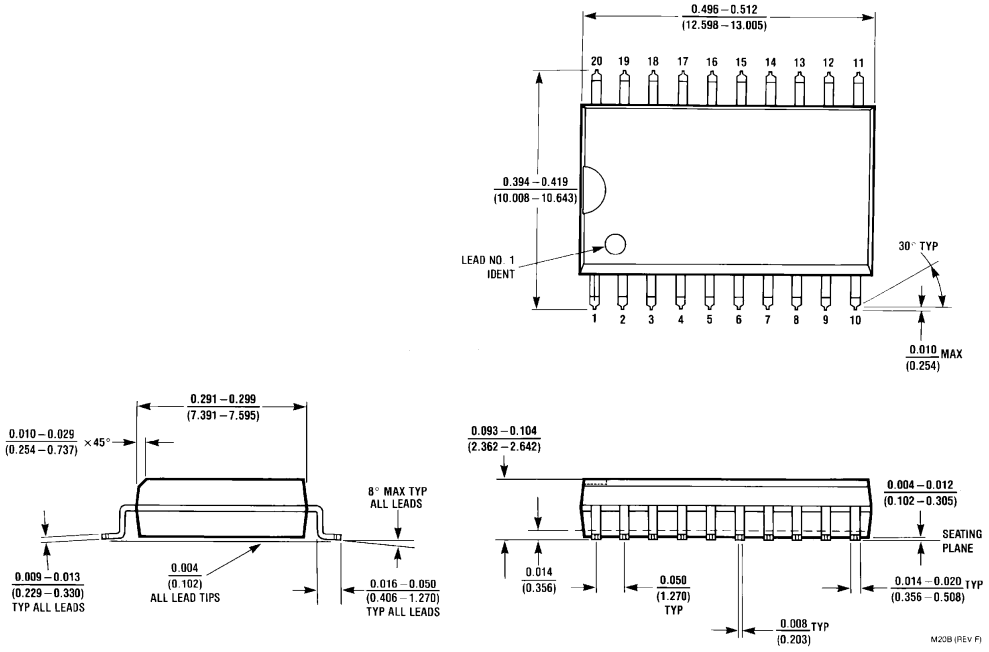
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0	6.7	9.0	4.0	12.0	4.0	10.0	ns
t_{PHL}	D_n to $\overline{O}_n$	2.5	4.4	7.0	2.5	9.0	2.5	8.0	
t_{PLH}	Propagation Delay	5.0	7.1	11.0	5.0	14.0	5.0	13.0	ns
t_{PHL}	LE to $\overline{O}_n$	3.0	4.7	7.0	3.0	9.0	3.0	8.0	
t_{PZH}	Output Enable Time	2.0	5.9	10.0	2.0	12.5	2.0	11.0	ns
t_{PZL}		2.0	5.6	7.5	2.0	10.5	2.0	8.5	
t_{PHZ}	Output Disable Time	1.5	3.4	6.5	1.5	8.5	1.5	7.0	ns
t_{PLZ}		1.5	2.7	5.5	1.5	7.5	1.5	6.5	

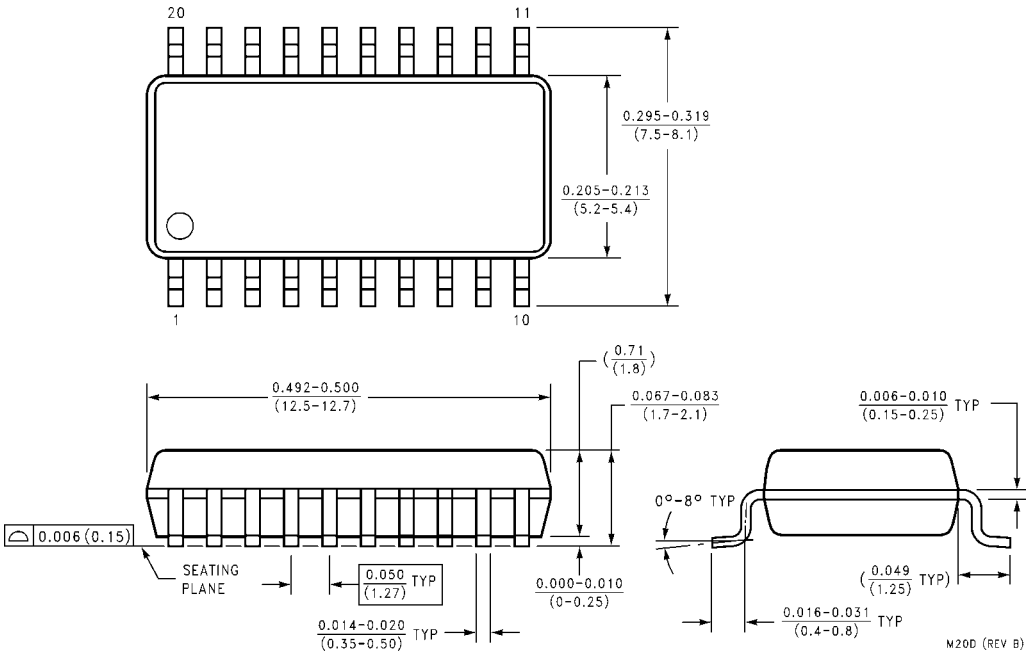
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_S(L)$	D_n to LE	2.0		2.0		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.0		3.0		ns
$t_H(L)$	D_n to LE	3.0		3.0		3.0		
$t_W(H)$	LE Pulse Width, HIGH	6.0		6.0		6.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

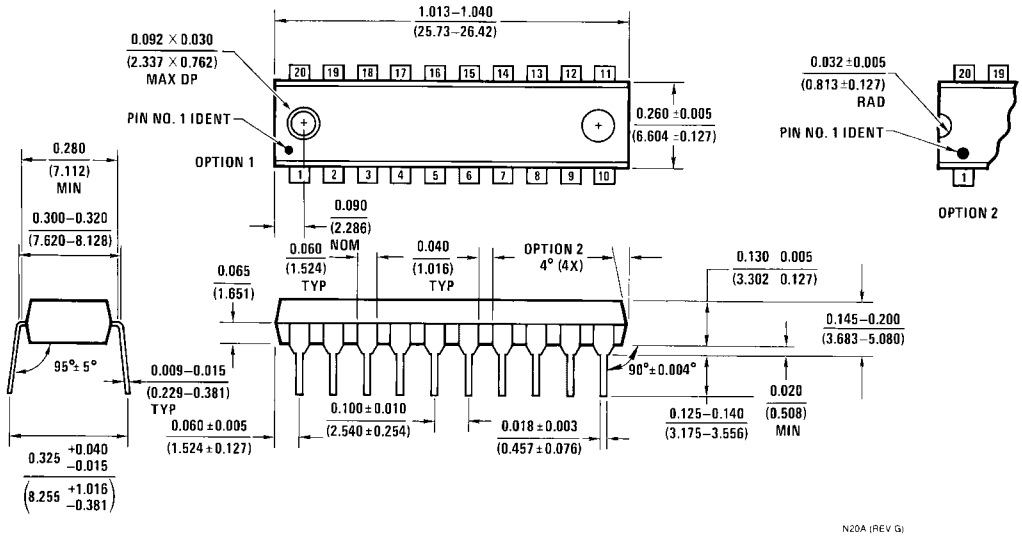


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F534
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The 74F534 is a high speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops. The 74F534 is the same as the 74F374 except that the outputs are inverted.

Features

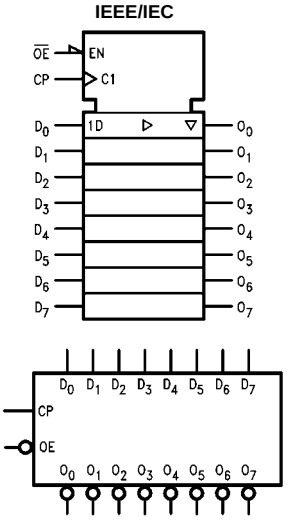
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- 3-STATE outputs for bus-oriented applications

Ordering Code:

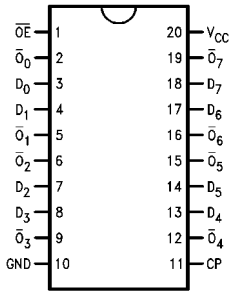
Order Number	Package Number	Package Description
74F534SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F534SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F534PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_0$–$\overline{O}_7$	Complementary 3-STATE Outputs	150/40(33.3)	–3 mA/24 mA (20 mA)

Function Table

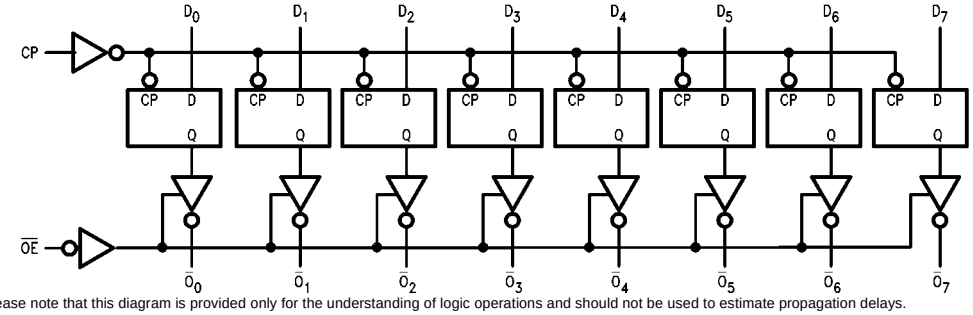
Inputs			Output
CP	$\overline{OE}$	D	$\overline{O}$
⌐	L	H	L
⌐	L	L	H
L	L	X	$\overline{O}_0$
X	H	X	Z

H = HIGH Voltage Level L = LOW Voltage Level
X = Immaterial Z = High Impedance
⌐ = LOW-to-HIGH Clock Transition
$\overline{O}_0$ = Value stored from previous clock cycle

Functional Description

The 74F534 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE complementary outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 1.50 µA All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			55	86	mA	Max	V_O = HIGH Z

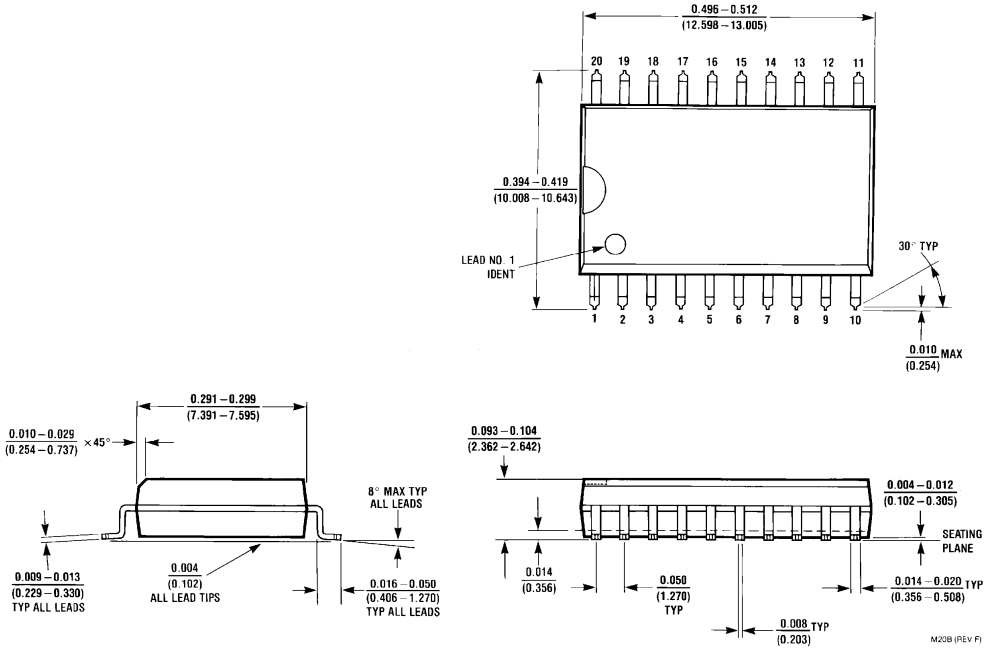
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100			60		70		MHz
t_{PLH}	Propagation Delay	4.0	6.5	8.5	4.0	10.5	4.0	10.0	ns
t_{PHL}	CP to $\overline{O}_n$	4.0	6.5	8.5	4.0	11.0	4.0	10.0	
t_{PZH}	Output Enable Time	2.0	9.0	11.5	2.0	14.0	2.0	12.5	ns
t_{PZL}		2.0	5.8	7.5	2.0	10.0	2.0	8.5	
t_{PHZ}	Output Disable Time	1.5	5.3	7.0	1.5	8.0	1.5	8.0	ns
t_{PLZ}		1.5	4.3	5.5	1.5	7.5	1.5	6.5	

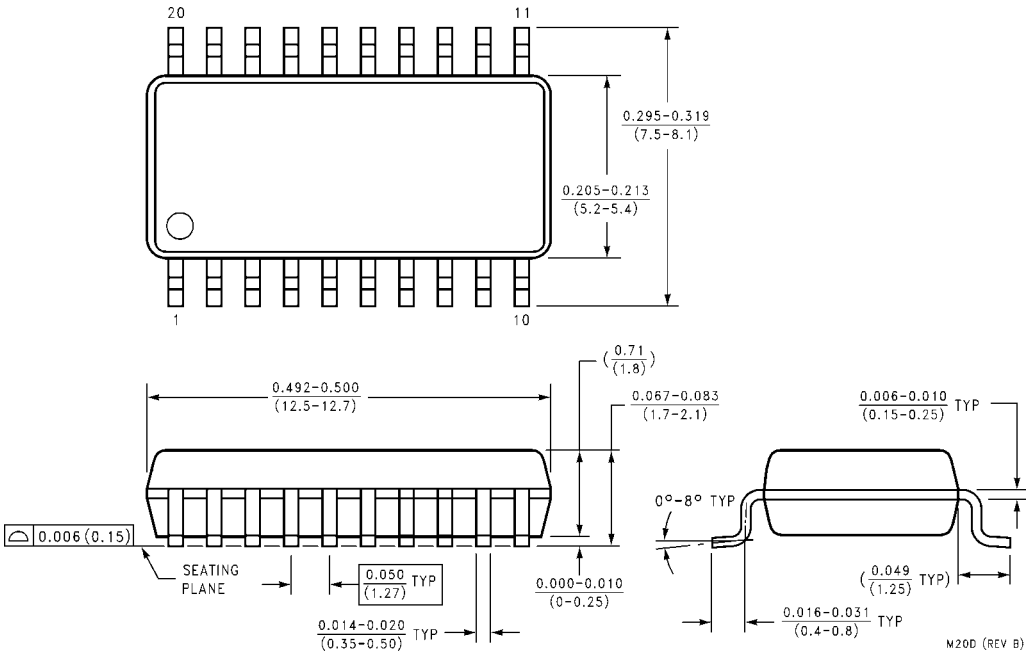
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_S(L)$	D_n to CP	2.0		2.5		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_H(L)$	D_n to CP	2.0		2.5		2.0		
$t_W(H)$	CP Pulse Width	7.0		7.0		7.0		ns
$t_W(L)$	HIGH or LOW	6.0		6.0		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted

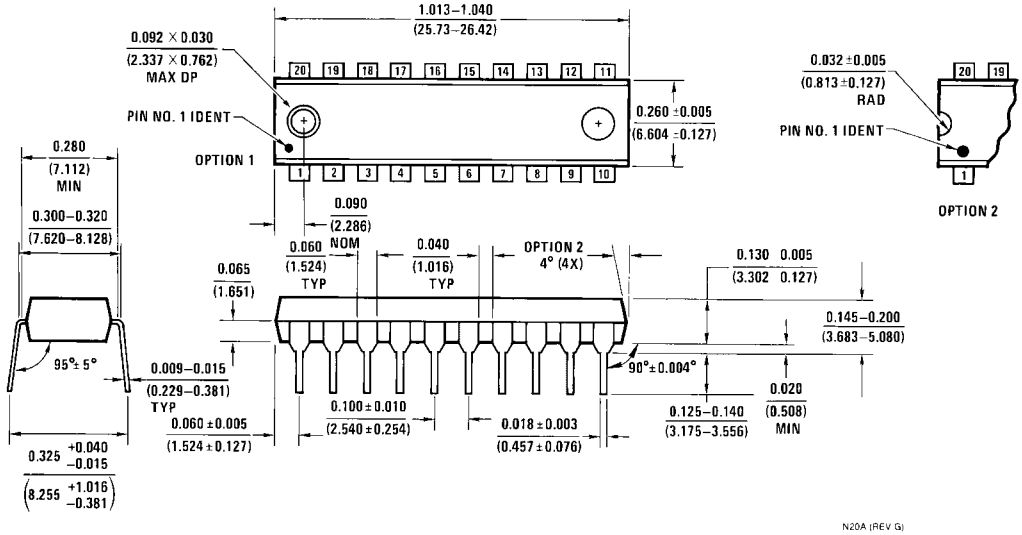


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F537
1-of-10 Decoder with 3-STATE Outputs

General Description

The 74F537 is one-of-ten decoder/demultiplexer with four active HIGH BCD inputs and ten mutually exclusive outputs. A polarity control input determines whether the outputs are active LOW or active HIGH. The 74F537 has 3-STATE outputs, and a HIGH signal on the Output Enable ($\overline{OE}$) input forces all outputs to the high impedance state.

Two input enables, active HIGH E_2 and active LOW $\overline{E}_1$, are available for demultiplexing data to the selected output in either non-inverted or inverted form. Input codes greater than BCD nine cause all outputs to go to the inactive state (i.e., same polarity as the P input).

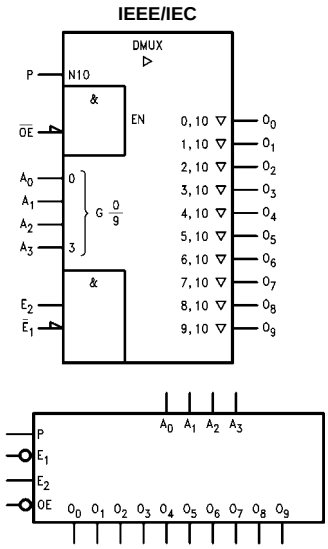
Ordering Code:

Order Number	Package Number	Package Description
74F537SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F537PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

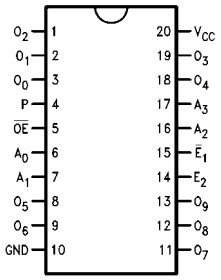
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols

IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

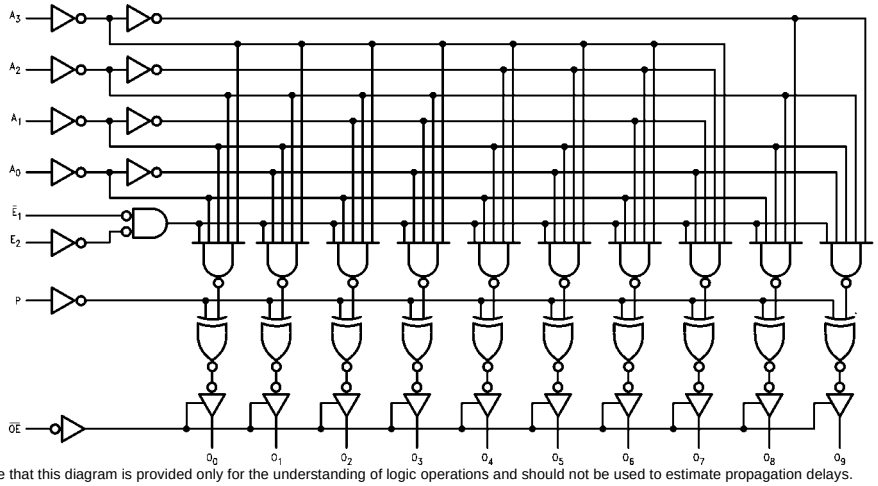
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	Address Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{E}_1$	Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
E_2	Enable Input (Active HIGH)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
P	Polarity Control Input	1.0/1.0	20 μA/–0.6 mA
O_0–O_9	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Truth Table

Function	Inputs									Outputs								
	$\overline{OE}$	$\overline{E}_1$	E_2	A_3	A_2	A_1	A_0	O_0	O_1	O_2	O_3	O_4	O_5	O_6	O_7	O_8	O_9
High Impedance	H	X	X	X	X	X	X	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z
Disable	L	H	X	X	X	X	X			Outputs Equal P Input								
	L	X	L	X	X	X	X											
Active HIGH	L	L	H	L	L	L	L	H	L	L	L	L	L	L	L	L	L	
Output	L	L	H	L	L	L	H	L	H	L	L	L	L	L	L	L	L	
(P = L)	L	L	H	L	L	H	L	L	L	H	L	L	L	L	L	L	L	
	L	L	H	L	L	H	H	L	L	L	H	L	L	L	L	L	L	
	L	L	H	L	H	L	L	L	L	L	L	H	L	L	L	L	L	
	L	L	H	L	H	L	H	L	L	L	L	L	H	L	L	L	L	
	L	L	H	L	H	H	L	L	L	L	L	L	L	H	L	L	L	
	L	L	H	L	H	H	H	L	L	L	L	L	L	L	H	L	L	
	L	L	H	H	L	L	L	L	L	L	L	L	L	L	L	H	L	
	L	L	H	H	L	L	H	L	L	L	L	L	L	L	L	L	H	
	L	L	H	H	X	H	X	L	L	L	L	L	L	L	L	L	L	
	L	L	H	H	H	X	X	L	L	L	L	L	L	L	L	L	L	
Active LOW	L	L	H	L	L	L	L	L	H	H	H	H	H	H	H	H	H	
Output	L	L	H	L	L	L	H	H	L	H	H	H	H	H	H	H	H	
(P = H)	L	L	H	L	L	H	L	H	H	L	H	H	H	H	H	H	H	
	L	L	H	L	L	H	H	H	H	H	L	H	H	H	H	H	H	
	L	L	H	L	H	L	L	H	H	H	H	L	H	H	H	H	H	
	L	L	H	L	H	L	H	H	H	H	H	H	L	H	H	H	H	
	L	L	H	L	H	H	L	H	H	H	H	H	H	L	H	H	H	
	L	L	H	L	H	H	H	H	H	H	H	H	H	H	L	H	H	
	L	L	H	H	L	L	L	H	H	H	H	H	H	H	H	L	H	
	L	L	H	H	L	L	H	H	H	H	H	H	H	H	H	H	L	
	L	L	H	H	X	H	X	H	H	H	H	H	H	H	H	H	H	
	L	L	H	H	H	X	X	H	H	H	H	H	H	H	H	H	H	

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

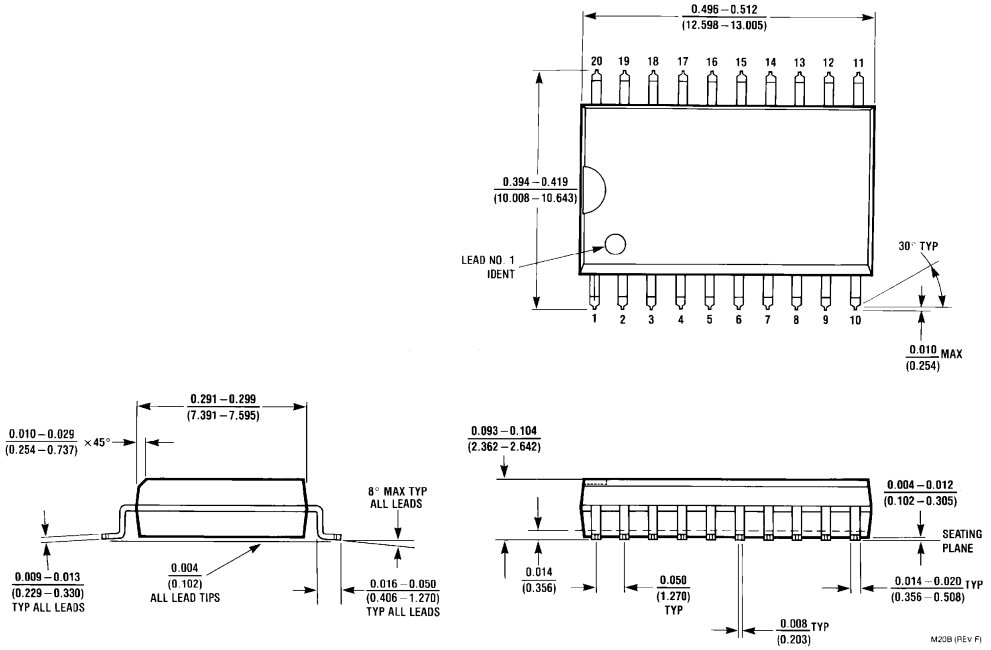
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current				56	mA	Max	V_O = HIGH
I_{CCZ}	Power Supply Current			44	66	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

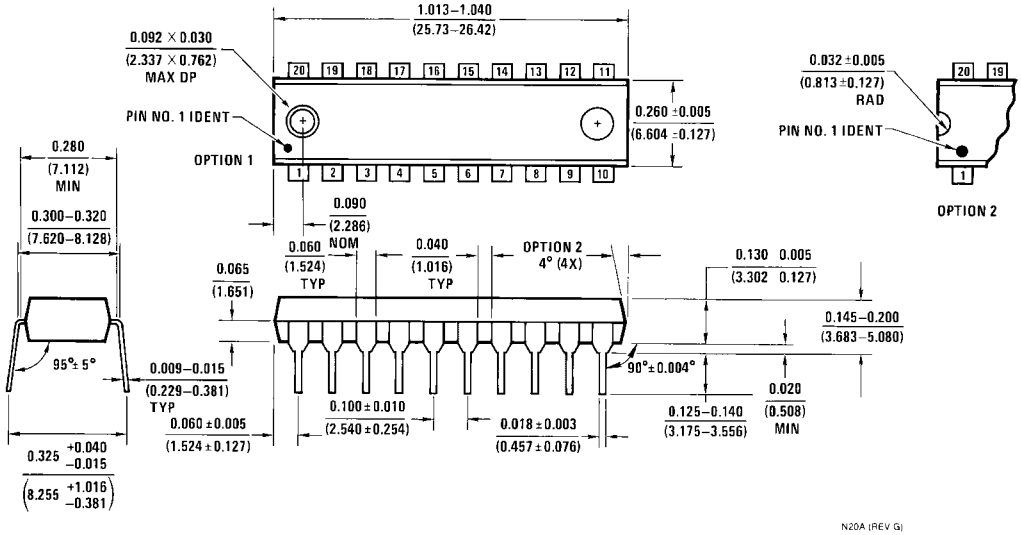
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	6.0	11.0	16.0	6.0	17.0	ns
t_{PHL}	A_n to O_n	4.0	7.5	11.0	4.0	12.0	
t_{PLH}	Propagation Delay	5.0	8.5	14.5	5.0	15.5	
t_{PHL}	$\overline{E}_1$ to O_n	4.0	6.5	9.0	4.0	10.0	
t_{PLH}	Propagation Delay	6.0	11.0	16.0	6.0	17.0	ns
t_{PHL}	E_2 to O_n	5.0	10.0	14.0	5.0	15.0	
t_{PLH}	Propagation Delay	6.0	11.5	18.0	6.0	20.0	
t_{PHL}	P to O_n	6.0	11.0	16.0	6.0	17.0	
t_{PZH}	Output Enable Time	3.0	5.5	10.5	3.0	11.5	ns
t_{PZL}	$\overline{OE}$ to O_n	5.0	9.0	13.0	5.0	14.0	
t_{PHZ}	Output Disable Time	2.0	4.0	6.0	2.0	7.0	
t_{PLZ}	$\overline{OE}$ to O_n	3.0	5.0	7.0	3.0	8.0	

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F538
1-of-8 Decoder with 3-STATE Outputs

General Description

The 74F538 decoder/demultiplexer accepts three Address (A_0–A_2) input signals and decodes them to select one of eight mutually exclusive outputs. A polarity control input (P) determines whether the outputs are active LOW or active HIGH. A HIGH Signal on either of the active LOW Output Enable ($\overline{OE}$) inputs forces all outputs to the high impedance state. Two active HIGH and two active LOW input enables are available for easy expansion to 1-of 32 decoding with four packages, or for data demultiplexing to 1-of-8 or 1-of-16 destinations.

Features

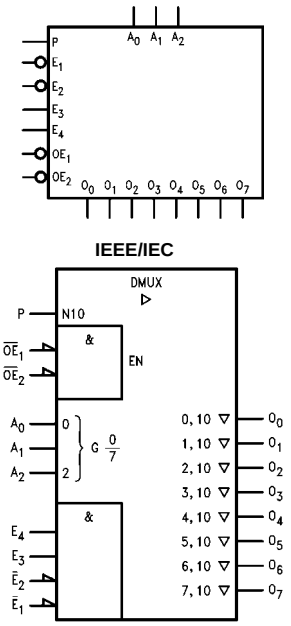
- Output polarity control
- Data demultiplexing capability
- Multiple enables for expansion
- 3-STATE outputs

Ordering Code:

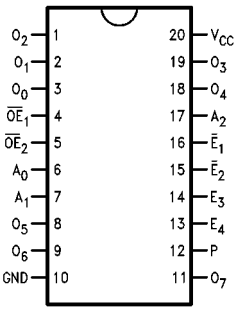
Order Number	Package Number	Package Description
74F538SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F538SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F538PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

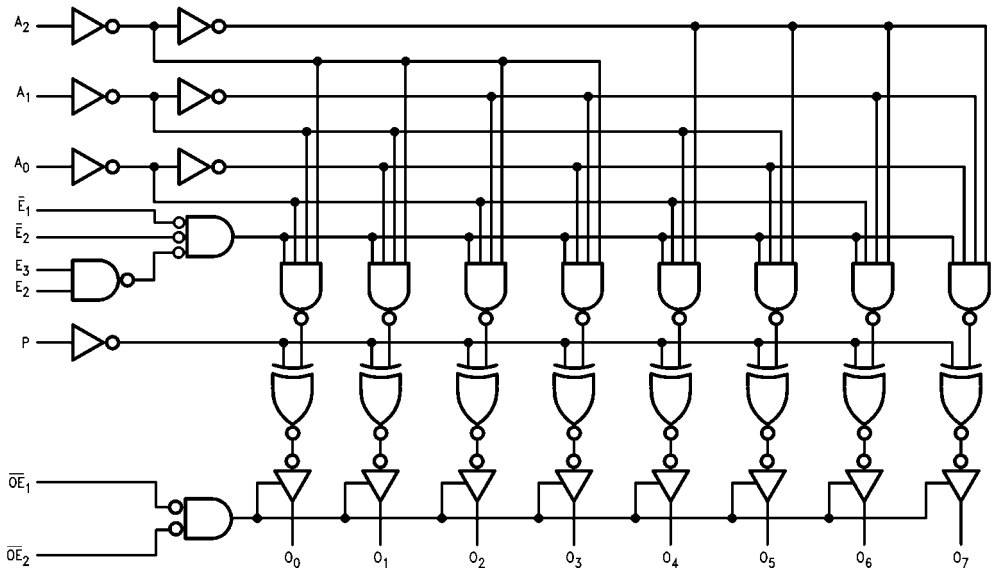
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_2	Address Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{E}_1$, $\overline{E}_2$	Enable Inputs (Active LOW)	1.0/1.0	20 μA/–0.6 mA
E_3, E_4	Enable Inputs (Active HIGH)	1.0/1.0	20 μA/–0.6 mA
P	Polarity Control Input	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Inputs (Active LOW)	1.0/1.0	20 μA/–0.6 mA
O_0–O_7	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Truth Table

Function	Inputs									Outputs							
	$\overline{OE}_1$	$\overline{OE}_2$	$\overline{E}_1$	E_2	E_3	E_4	A_2	A_1	A_0	O_0	O_1	O_2	O_3	O_4	O_5	O_6	O_7
High	H	X	X	X	X	X	X	X	X	Z	Z	Z	Z	Z	Z	Z	Z
Impedance	X	H	X	X	X	X	X	X	X	Z	Z	Z	Z	Z	Z	Z	Z
Disable	L	L	H	X	X	X	X	X	X								
	L	L	X	H	X	X	X	X	X				Outputs Equal P Input				
	L	L	X	X	L	X	X	X	X								
	L	L	X	X	X	L	X	X	X								
Active HIGH	L	L	L	L	H	H	L	L	L	H	L	L	L	L	L	L	L
Output	L	L	L	L	H	H	L	L	H	L	H	L	L	L	L	L	L
(P = L)	L	L	L	L	H	H	L	H	L	L	L	H	L	L	L	L	L
	L	L	L	L	H	H	L	H	H	L	L	L	H	L	L	L	L
	L	L	L	L	H	H	H	L	L	L	L	L	L	H	L	L	L
	L	L	L	L	H	H	H	L	H	L	L	L	L	L	H	L	L
	L	L	L	L	H	H	H	H	L	L	L	L	L	L	L	H	L
	L	L	L	L	H	H	H	H	H	L	L	L	L	L	L	L	H
Active LOW	L	L	L	L	H	H	L	L	L	L	H	H	H	H	H	H	H
Output	L	L	L	L	H	H	L	L	H	H	L	H	H	H	H	H	H
(P = H)	L	L	L	L	H	H	L	H	L	H	H	L	H	H	H	H	H
	L	L	L	L	H	H	L	H	H	H	H	H	L	H	H	H	H
	L	L	L	L	H	H	H	L	L	H	H	H	H	L	H	H	H
	L	L	L	L	H	H	H	L	H	H	H	H	H	H	L	H	H
	L	L	L	L	H	H	H	H	L	H	H	H	H	H	H	L	H
	L	L	L	L	H	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

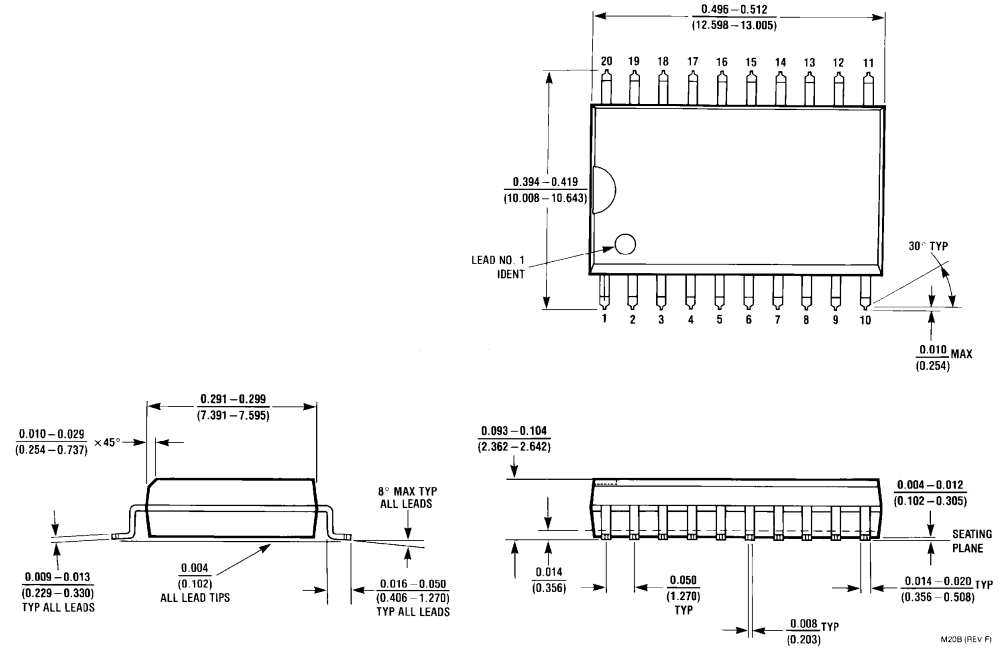
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			31	45	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			37	56	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			37	56	mA	Max	V_O = HIGH Z

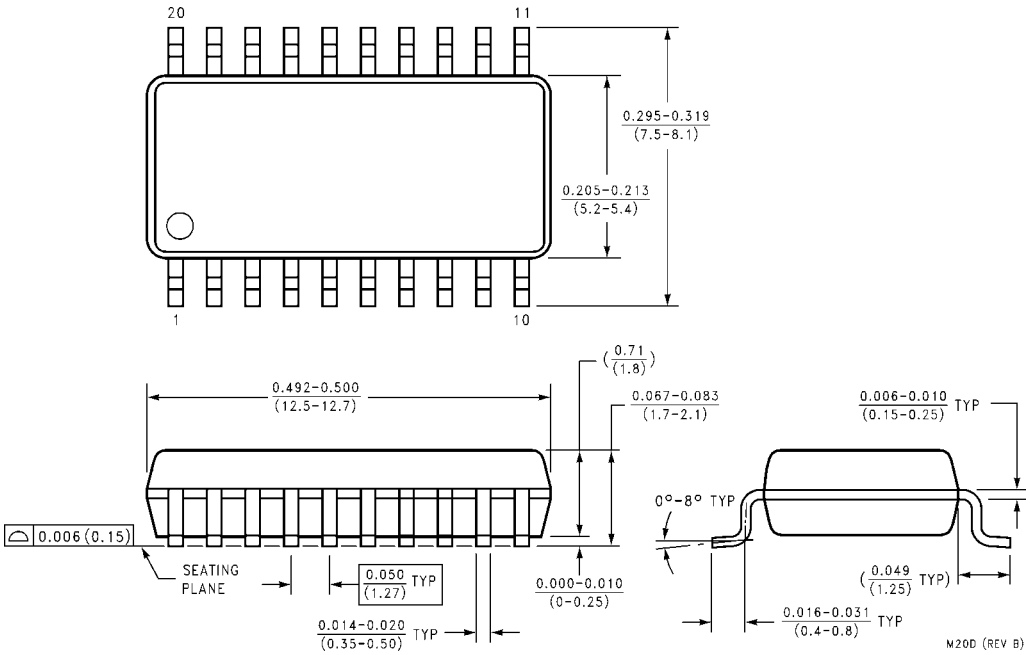
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	6.0	11.0	16.0	6.0	17.0	ns
t_{PHL}	A_n to O_n	4.0	7.5	11.0	4.0	12.0	
t_{PLH}	Propagation Delay	5.0	8.5	15.0	5.0	16.0	ns
t_{PHL}	$\overline{E}_1$ or $\overline{E}_2$ to O_n	4.0	6.5	9.0	4.0	10.0	
t_{PLH}	Propagation Delay	6.0	11.0	16.0	6.0	17.0	ns
t_{PHL}	E_3 or E_4 to O_n	5.0	10.0	14.0	5.0	15.0	
t_{PLH}	Propagation Delay	6.0	11.5	18.0	6.0	20.0	ns
t_{PHL}	P to O_n	6.0	11.0	16.0	6.0	17.0	
t_{PZH}	Output Enable Time	3.0	5.5	10.0	3.0	11.0	ns
t_{PZL}	$\overline{OE}_1$ or $\overline{OE}_2$ to O_n	5.0	9.0	13.0	5.0	14.0	
t_{PHZ}	Output Disable Time	2.0	4.0	6.0	2.0	7.0	ns
t_{PLZ}	$\overline{OE}_1$ or $\overline{OE}_2$ to O_n	3.0	5.0	8.0	3.0	9.0	

Physical Dimensions inches (millimeters) unless otherwise noted

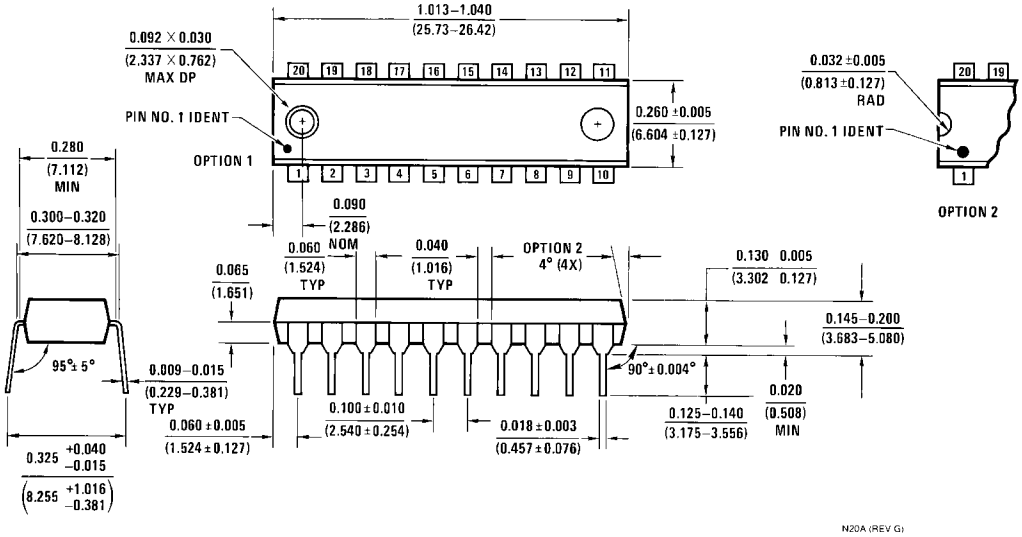


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F539
Dual 1-of-4 Decoder with 3-STATE Outputs

General Description

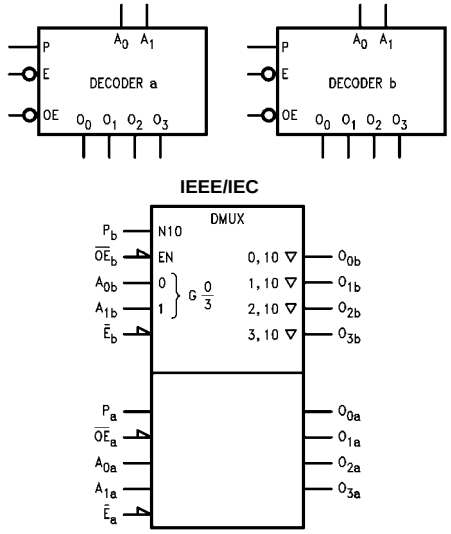
The 74F539 contains two independent decoders. Each accepts two Address (A_0, A_1) input signals and decodes them to select one of four mutually exclusive outputs. A polarity control input (P) determines whether the outputs are active HIGH (P = L) or active LOW (P = H). An active LOW input Enable ($\overline{E}$) is available for data demultiplexing; data is routed to the selected output in non-inverted form in the active LOW mode or in inverted form in the active HIGH mode. A HIGH signal on the active LOW Output Enable ($\overline{OE}$) input forces the 3-STATE outputs to the high impedance state.

Ordering Code:

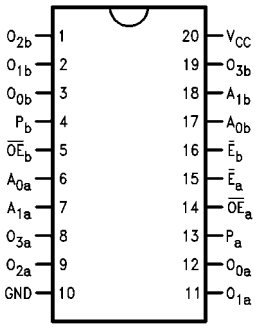
Order Number	Package Number	Package Description
74F539SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F539PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_{0a}–A_{1a}	Side A Address Inputs	1.0/1.0	20 µA/–0.6 mA
A_{0b}–A_{1b}	Side B Address Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{E}_a$, $\overline{E}_b$	Enable Inputs (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}_a$, $\overline{OE}_b$	Output Enable Inputs (Active LOW)	1.0/1.0	20 µA/–0.6 mA
P_a, P_b	Polarity Control Inputs	1.0/1.0	20 µA/–0.6 mA
O_{0a}–O_{3a}	Side A 3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)
O_{0b}–O_{3b}	Side B 3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

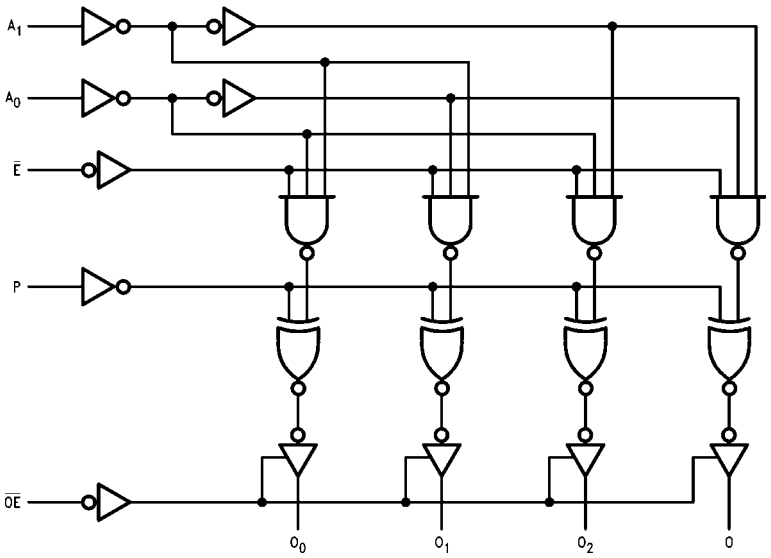
Truth Table

(each half)

Function	Inputs				Outputs			
	$\overline{OE}$	$\overline{E}$	A_1	A_0	O_0	O_1	O_2	O_3
High Impedance	H	X	X	X	Z	Z	Z	Z
Disable	L	H	X	X	$O_n = P$			
Active HIGH	L	L	L	L	H	L	L	L
Output	L	L	L	H	L	H	L	L
(P = L)	L	L	H	L	L	L	H	L
	L	L	H	H	L	L	L	H
Active LOW	L	L	L	L	L	H	H	H
Output	L	L	L	H	H	L	H	H
(P = H)	L	L	H	L	H	H	L	H
	L	L	H	H	H	H	H	L

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Logic Diagram (one half shown)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

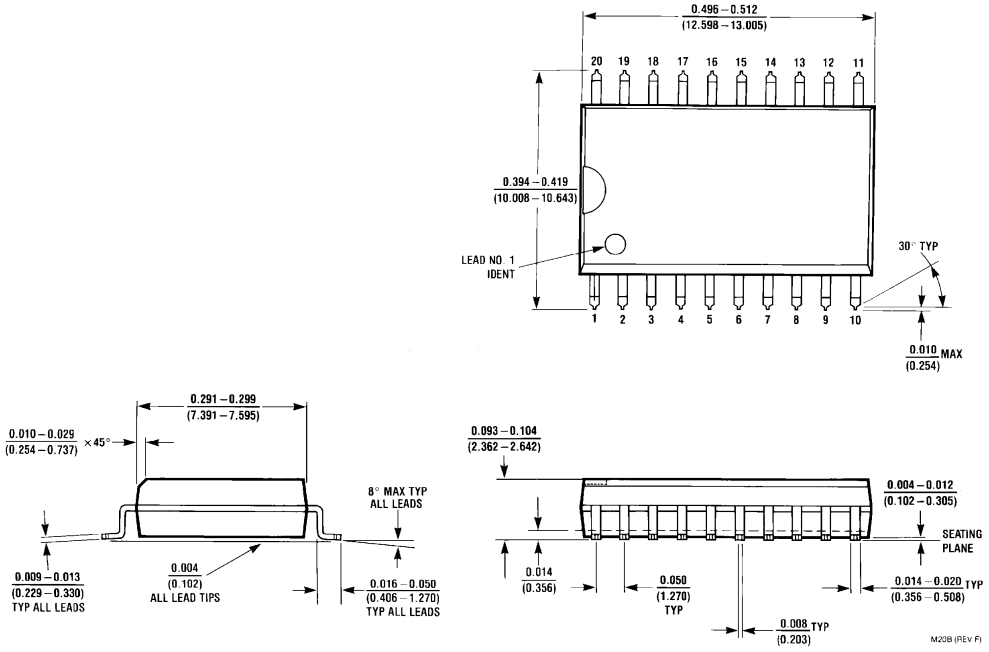
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			28	45	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			40	60	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			40	60	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

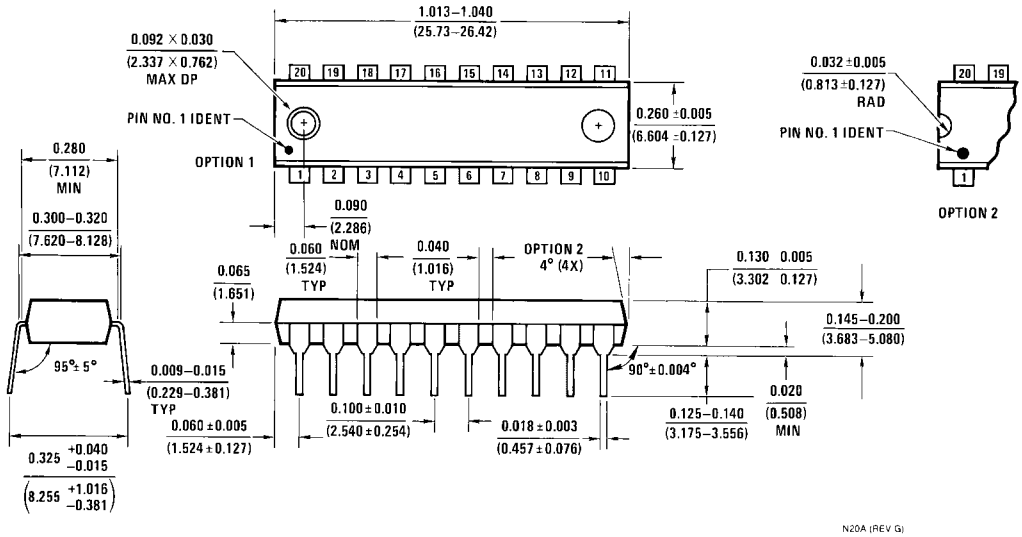
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	4.0	14.5	18.5	3.5	19.5	ns
t_{PHL}	A_n to O_n	4.0	9.5	12.0	4.0	13.0	
t_{PLH}	Propagation Delay	5.0	12.0	16.0	5.5	17.0	ns
t_{PHL}	$\overline{E}$ to O_n	4.0	7.5	9.5	4.0	10.5	
t_{PLH}	Propagation Delay	7.5	14.5	21.5	4.5	22.5	ns
t_{PHL}	P to O_n	5.0	11.0	16.5	4.5	17.5	
t_{PZH}	Output Enable Time	4.5	8.0	10.5	4.0	11.5	ns
t_{PZL}	$\overline{OE}$ to O_n	5.5	10.0	13.0	5.0	14.0	
t_{PHZ}	Output Disable Time	2.0	4.5	6.5	2.0	7.0	
t_{PLZ}	$\overline{OE}$ to O_n	3.0	6.5	8.5	3.0	9.5	

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F540 • 74F541
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The 74F540 and 74F541 are similar in function to the 74F240 and 74F244 respectively, except that the inputs and outputs are on opposite sides of the package (see Connection Diagrams). This pinout arrangement makes these devices especially useful as output ports for microprocessors, allowing ease of layout and greater PC board density.

Features

- 3-STATE outputs drive bus lines
- Inputs and outputs opposite side of package, allowing easier interface to microprocessors

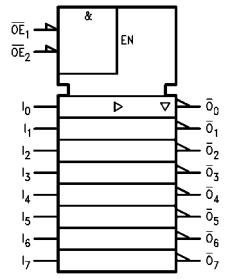
Ordering Code:

Order Number	Package Number	Package Description
74F540SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F540SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F540PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F541SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F541PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

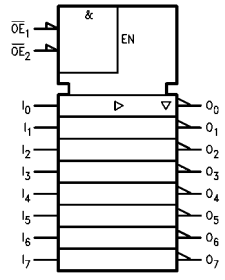
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols

IEEE/IEC
74F540

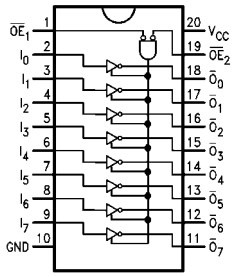


IEEE/IEC
74F541

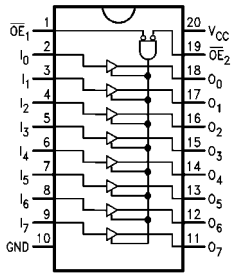


Connection Diagrams

74F540



74F541



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
I_n	Inputs	1.0/1.0	20 μA/–0.6 mA
O_n, $\overline{O}_n$	Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Truth Table

Inputs			Outputs	
$\overline{OE}_1$	$\overline{OE}_2$	I	74F540	74F541
L	L	H	L	H
H	X	X	Z	Z
X	H	X	Z	Z
L	L	L	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

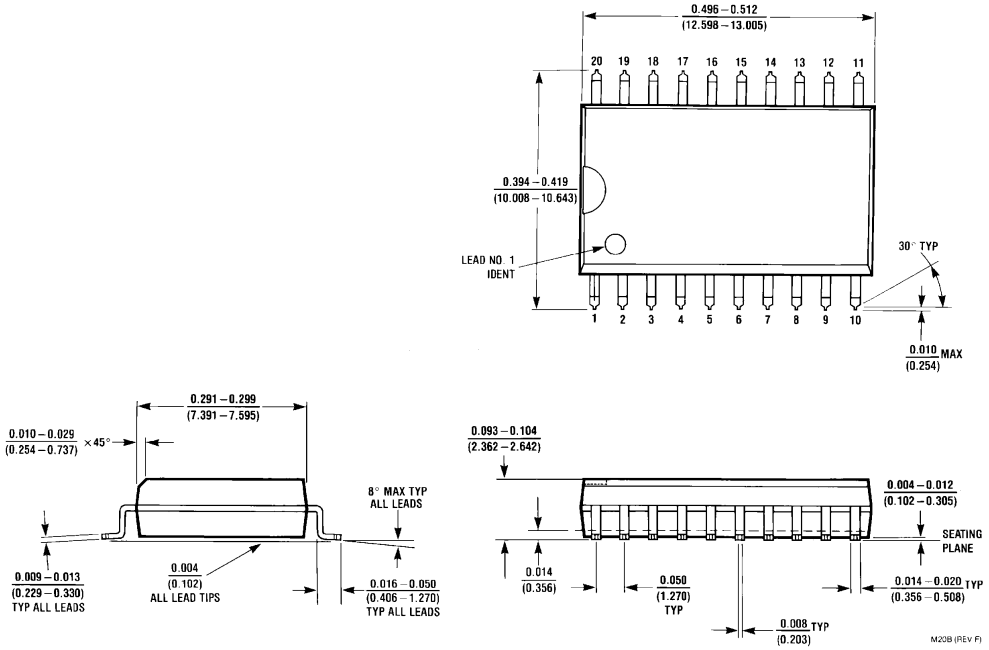
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		10% V_{CC}	2.0					I_{OH} = −15 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current ('74F540)			11	20	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F540)			53	75	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F540)			31	45	mA	Max	V_O = HIGH Z
I_{CCH}	Power Supply Current (74F541)			26	35	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F541)			55	75	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F541)			31	55	mA	Max	V_O = HIGH Z

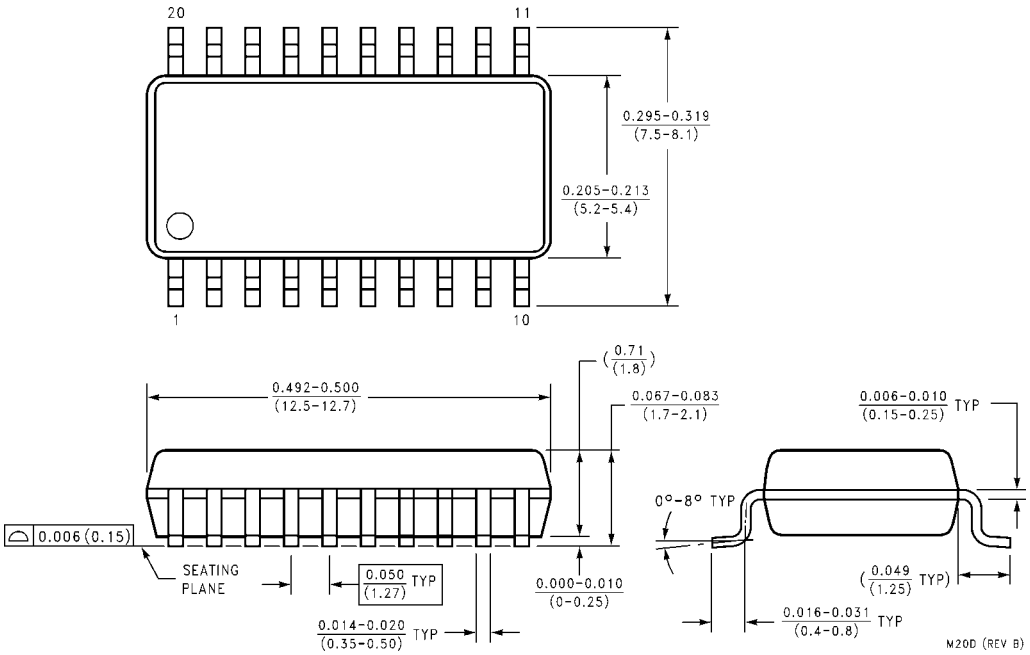
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	3.0	5.0	1.0	6.0	1.0	5.5	ns
t_{PHL}	Data to Output (74F540)	1.0	2.0	4.0	1.0	4.5	1.0	4.0	
t_{PZH}	Output Enable Time (74F540)	2.5	4.9	8.0	2.5	9.0	2.5	8.5	ns
t_{PZL}		3.5	5.8	10.0	3.5	11.0	3.5	10.5	
t_{PHZ}	Output Disable Time (74F540)	1.5	3.4	6.0	1.5	7.0	1.5	6.5	
t_{PLZ}		1.0	2.5	5.5	1.0	7.5	1.0	6.0	
t_{PLH}	Propagation Delay	1.5	3.3	5.5			1.5	6.0	ns
t_{PHL}	Data to Output (74F541)	1.5	2.7	5.5			1.5	6.0	
t_{PZH}	Output Enable Time (74F541)	3.0	5.8	8.0			2.5	9.5	ns
t_{PZL}		3.5	6.1	8.5			3.0	9.5	
t_{PHZ}	Output Disable Time (74F541)	1.5	3.4	6.0			1.5	6.5	
t_{PLZ}		1.5	2.9	5.5			1.5	6.0	

Physical Dimensions inches (millimeters) unless otherwise noted

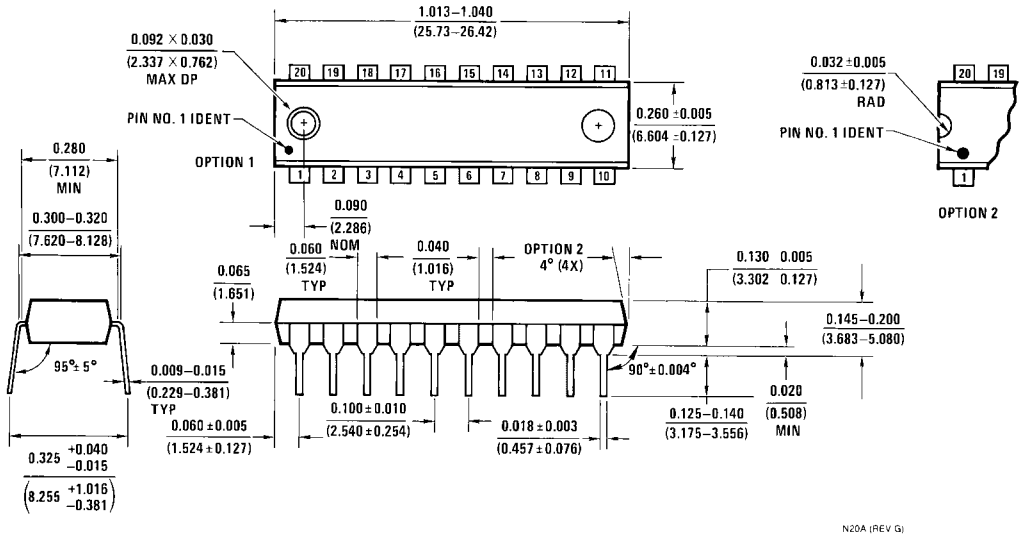


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised March 1999

74F543
Octal Registered Transceiver

General Description

The F543 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. The A outputs are guaranteed to sink 24 mA while the B outputs are rated for 64 mA.

Features

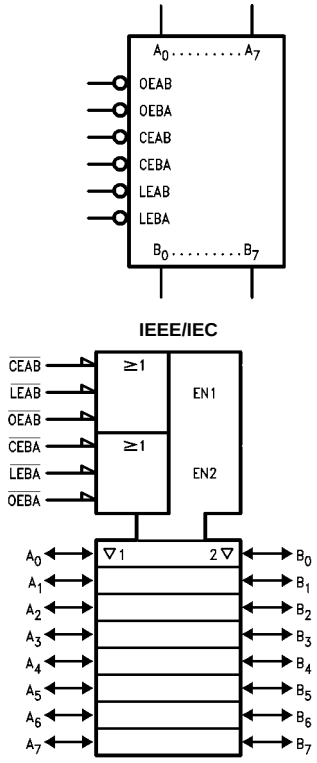
- 8-bit octal transceiver
- Back-to-back registers for storage
- Separate controls for data flow in each direction
- A outputs sink 24 mA
- B outputs sink 64 mA

Ordering Code:

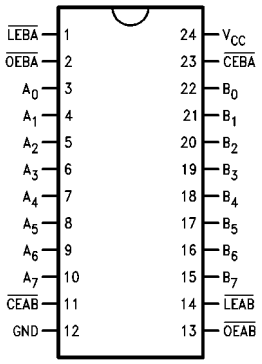
Order Number	Package Number	Package Description
74F543SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F543MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F543SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OEAB}$	A-to-B Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{OEBA}$	B-to-A Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{CEAB}$	A-to-B Enable Input (Active LOW)	1.0/2.0	20 μA/–1.2 mA
$\overline{CEBA}$	B-to-A Enable Input (Active LOW)	1.0/2.0	20 μA/–1.2 mA
$\overline{LEAB}$	A-to-B Latch Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{LEBA}$	B-to-A Latch Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
A_0–A_7	A-to-B Data Inputs or	3.5/1.083	70 μA/–650 μA
	B-to-A 3-STATE Outputs	150/40 (33.8)	–3 mA/24 mA (20 mA)
B_0–B_7	B-to-A Data Inputs or	3.5/1.083	70 μA/–650 μA
	A-to-B 3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Functional Description

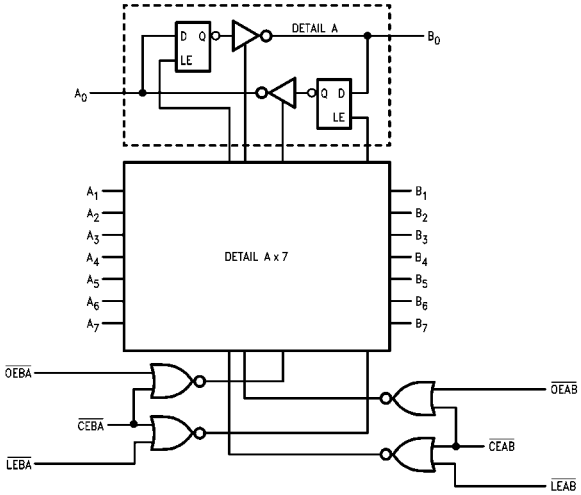
The F543 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from A_0–A_7 or take data from B_0–B_7, as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$ inputs.

Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5					I_{OH} = −1 mA (A_n)
		10% V_{CC}	2.4					I_{OH} = −3 mA (A_n, B_n)
		5% V_{CC}	2.7			V	Min	I_{OH} = −1 mA (A_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n)
		10% V_{CC}	2.0					I_{OH} = −15 mA (B_n)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA (A_n)
	Voltage	10% V_{CC}			0.55			I_{OL} = 64 mA (B_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	($\overline{OEAB}$, $\overline{OEBA}$, $\overline{LEAB}$, $\overline{LEBA}$, $\overline{CEAB}$, $\overline{CEBA}$)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V ($\overline{OEAB}$, $\overline{OEBA}$)
					−1.2			V_{IN} = 0.5V ($\overline{CEAB}$, $\overline{CEBA}$)
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V (A_n)
			−100		−225			V_{OUT} = 0V (B_n)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V (A_n, B_n)
I_{CCH}	Power Supply Current			67	100	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			83	125	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			83	125	mA	Max	V_O = HIGH Z

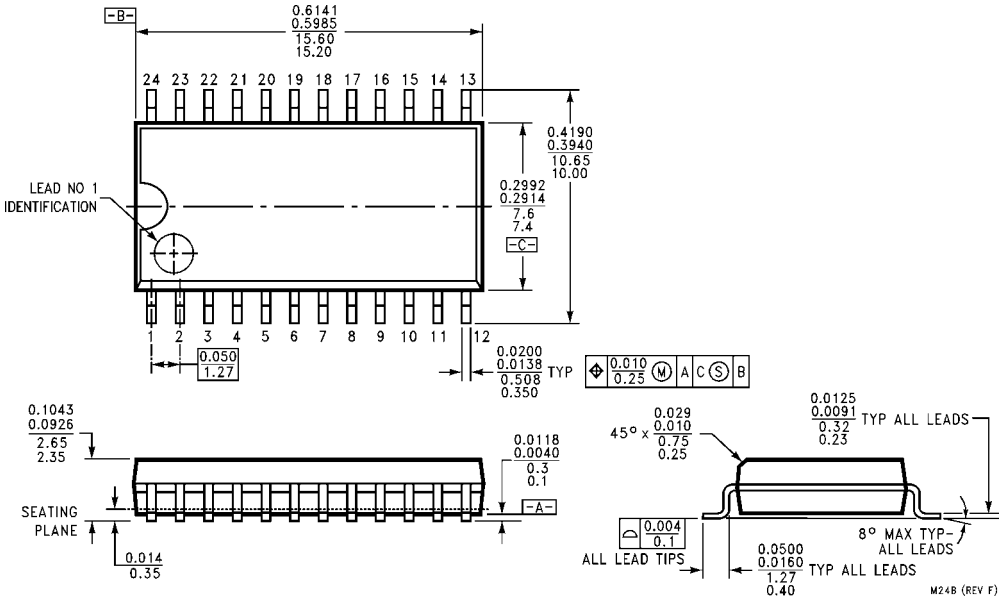
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	5.5	7.5	3.0	8.5	
t_{PHL}	Transparent Mode	3.0	5.0	6.5	3.0	7.5	ns
	A_n to B_n or B_n to A_n						
t_{PLH}	Propagation Delay	4.5	8.5	11.0	4.5	12.5	ns
t_{PHL}	$\overline{LEBA}$ to A_n	4.5	8.5	11.0	4.5	12.5	
t_{PLH}	Propagation Delay	4.5	8.5	11.0	4.5	12.5	ns
t_{PHL}	$\overline{LEAB}$ to B_n	4.5	8.5	11.0	4.5	12.5	
t_{PZH}	Output Enable Time						
t_{PZL}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	3.0	7.0	9.0	3.0	10.0	
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	4.0	7.5	10.5	4.0	12.0	ns
t_{PHZ}	Output Disable Time						
t_{PLZ}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.0	6.0	8.0	1.0	9.0	
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n	2.5	5.5	10.5	2.5	11.5	

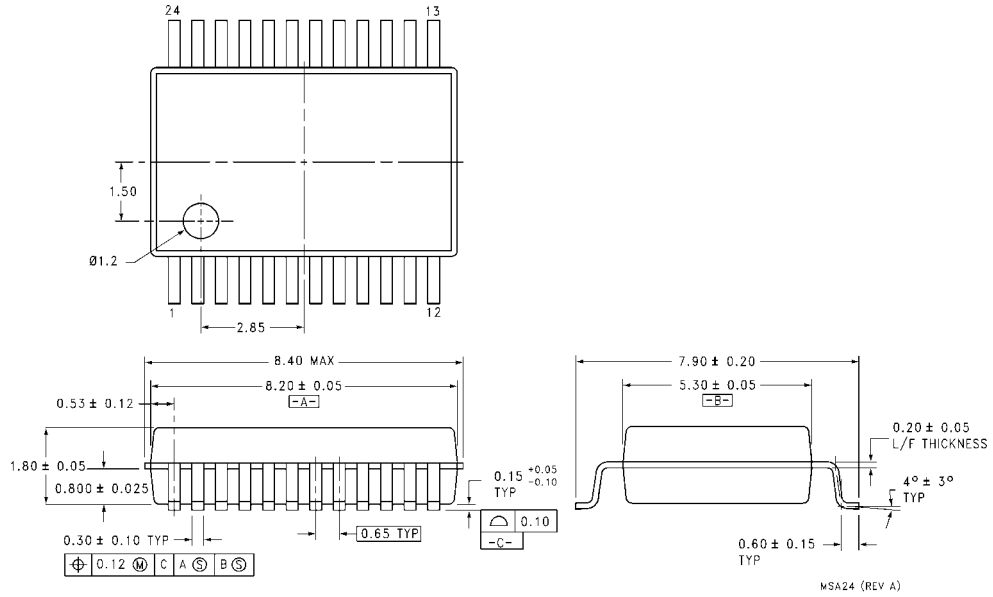
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.5		
$t_S(L)$	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	3.0		3.5		ns
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.5		
$t_H(L)$	A_n or B_n to $\overline{LEBA}$ or $\overline{LEAB}$	3.0		3.5		
$t_W(L)$	Latch Enable, B to A or	8.0		9.0		ns
	B to A Pulse Width, LOW					

Physical Dimensions inches (millimeters) unless otherwise noted

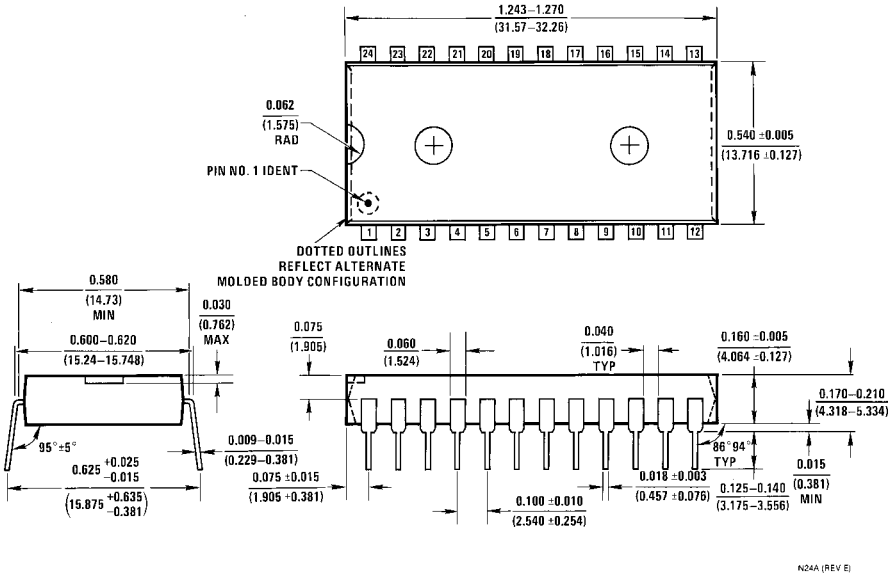


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



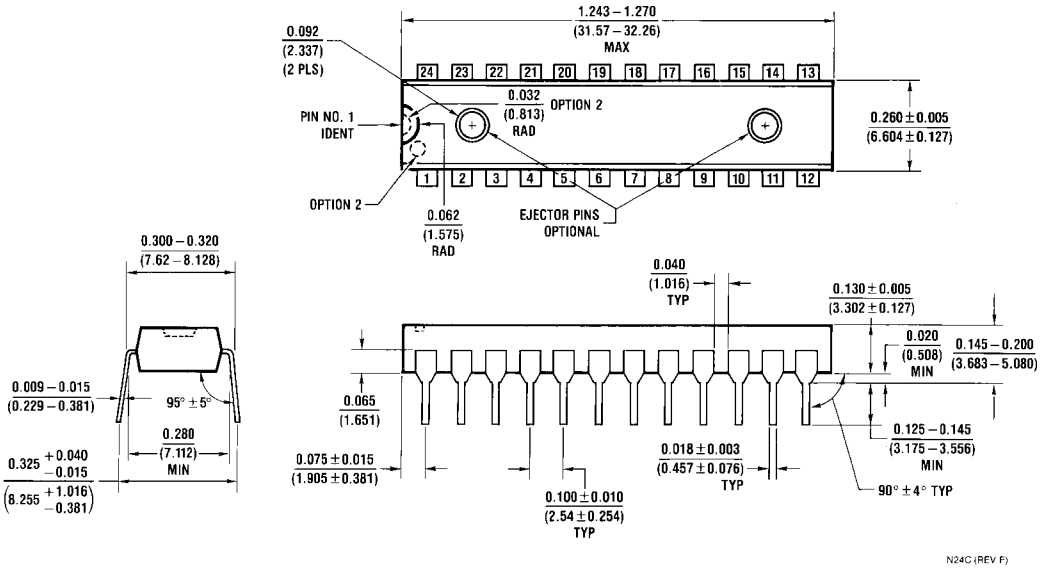
24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
Package Number N24A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F544
Octal Registered Transceiver

General Description

The 74F544 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. The A outputs are guaranteed to sink 24 mA while the B outputs are rated for 64 mA. The 74F544 inverts data in both directions.

Features

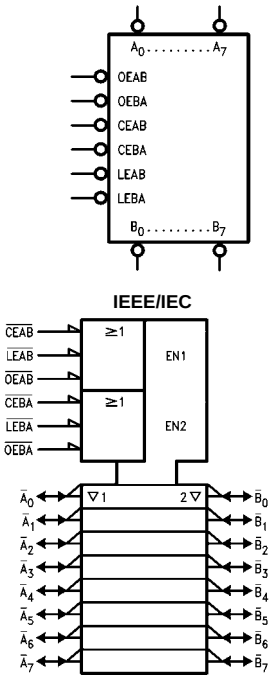
- 8-bit octal transceiver
- Back-to-back registers for storage
- Separate controls for data flow in each direction
- A outputs sink 24 mA, B outputs sink 64 mA

Ordering Code:

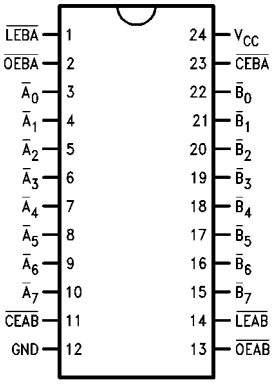
Order Number	Package Number	Package Description
74F544SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F544MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F544SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OEAB}$	A-to-B Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{OEBA}$	B-to-A Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{CEAB}$	A-to-B Enable Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
$\overline{CEBA}$	B-to-A Enable Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
$\overline{LEAB}$	A-to-B Latch Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{LEBA}$	B-to-A Latch Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{A}_0$–$\overline{A}_7$	A-to-B Data Inputs or	3.5/1.083	70 µA/–650 µA
	B-to-A 3-STATE Outputs	150/40(33.3)	–3 mA/24 mA (20 mA)
$\overline{B}_0$–$\overline{B}_7$	B-to-A Data Inputs or	3.5/1.083	70 µA/–650 µA
	A-to-B 3-STATE Outputs	600/106.6(80)	–12 mA/64 mA (48 mA)

Functional Description

The 74F544 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from $\overline{A}_0$–$\overline{A}_7$ or take data from $\overline{B}_0$–$\overline{B}_7$, as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$ inputs.

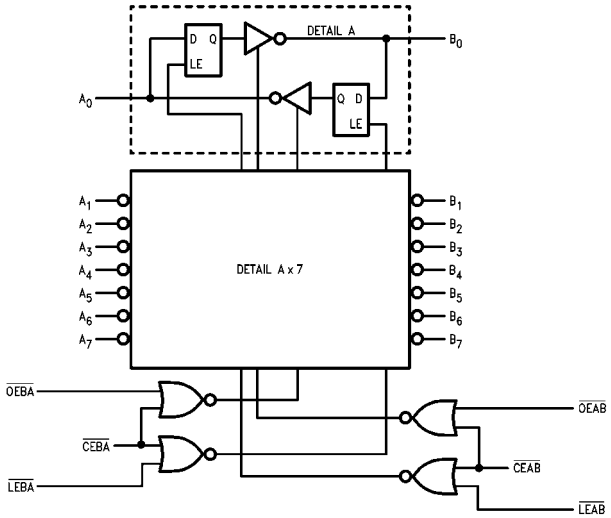
Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Note: A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA, (except $\overline{A}_n$, $\overline{B}_n$)
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA ($\overline{A}_n$)
		10% V_{CC}	2.4					I_{OH} = −3 mA ($\overline{A}_n$, $\overline{B}_n$)
		10% V_{CC}	2.0					I_{OH} = −15 mA ($\overline{B}_n$)
		5% V_{CC}	2.7					I_{OH} = −1 mA ($\overline{A}_n$)
		5% V_{CC}	2.7					I_{OH} = −3 mA ($\overline{A}_n$, $\overline{B}_n$)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA ($\overline{A}_n$)
		10% V_{CC}			0.55			I_{OL} = 64 mA ($\overline{B}_n$)
I_{IH}	Input HIGH Current				20.0	µA	Max	V_{IN} = 2.7V (except $\overline{A}_n$, $\overline{B}_n$)
					5.0			
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (except $\overline{A}_n$, $\overline{B}_n$)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V ($\overline{A}_n$, $\overline{B}_n$)
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC} ($\overline{A}_n$, $\overline{B}_n$)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V ($\overline{OEAB}$, $\overline{OEBA}$)
					−1.2			V_{IN} = 0.5V ($\overline{CEAB}$, $\overline{CEBA}$)
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V ($\overline{A}_n$, $\overline{B}_n$)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V ($\overline{A}_n$, $\overline{B}_n$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V ($\overline{A}_n$)
			−100		−225			V_{OUT} = 0V ($\overline{B}_n$)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V ($\overline{A}_n$, $\overline{B}_n$)
I_{CCH}	Power Supply Current			70	105	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			85	130	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			83	125	mA	Max	V_O = HIGH Z

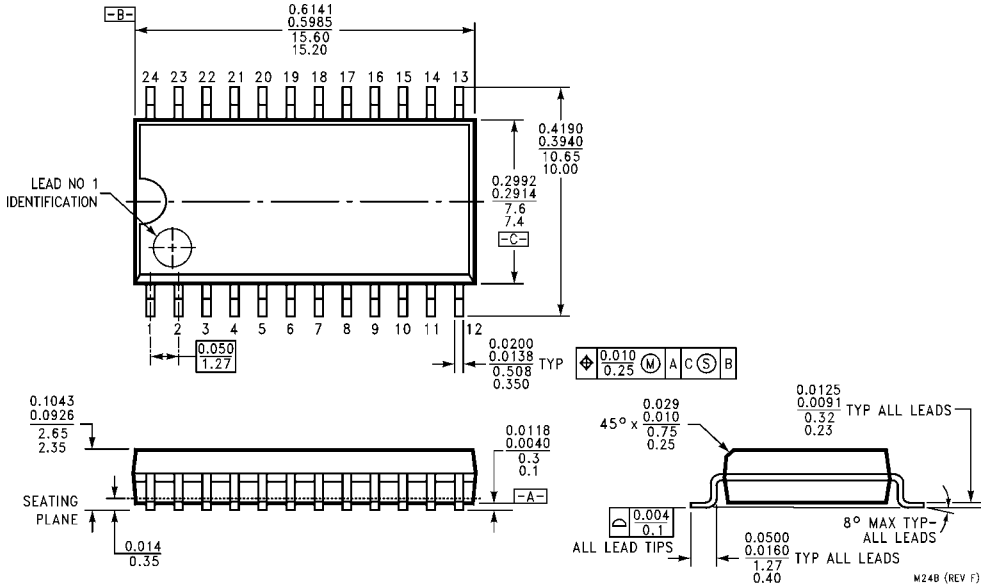
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	7.0	9.5	3.0	12.0	3.0	10.5	ns
t_{PHL}	Transparent Mode	3.0	5.0	6.5	2.5	8.5	3.0	7.5	
	$\overline{A}_n$ to $\overline{B}_n$ or $\overline{B}_n$to $\overline{A}_n$								
t_{PLH}	Propagation Delay	6.0	10.0	13.0	6.0	18.0	6.0	14.5	ns
t_{PHL}	$\overline{LEBA}$ to $\overline{A}_n$	4.0	7.0	9.5	4.0	11.5	4.0	10.5	
t_{PLH}	Propagation Delay	6.0	10.0	13.0	6.0	18.0	6.0	14.5	ns
t_{PHL}	$\overline{LEAB}$ to $\overline{B}_n$	4.0	7.0	9.5	4.0	11.5	4.0	10.5	
t_{PZH}	Output Enable Time	3.0	7.0	9.0	3.0	11.0	3.0	10.0	ns
t_{PZL}	$\overline{OEBA}$ or $\overline{OEAB}$ to $\overline{A}_n$ or $\overline{B}_n$	4.0	7.5	10.5	4.0	13.0	4.0	12.0	
	$\overline{CEBA}$ or $\overline{CEAB}$ to $\overline{A}_n$ or $\overline{B}_n$								
t_{PHZ}	Output Disable Time	1.0	6.0	8.0	2.0	10.0	1.0	9.0	
t_{PLZ}	$\overline{OEBA}$ or $\overline{OEAB}$ to $\overline{A}_n$ or $\overline{B}_n$	2.5	5.5	10.5	2.0	9.5	2.5	11.5	
	$\overline{CEBA}$ or $\overline{CEAB}$ to $\overline{A}_n$ or $\overline{B}_n$								

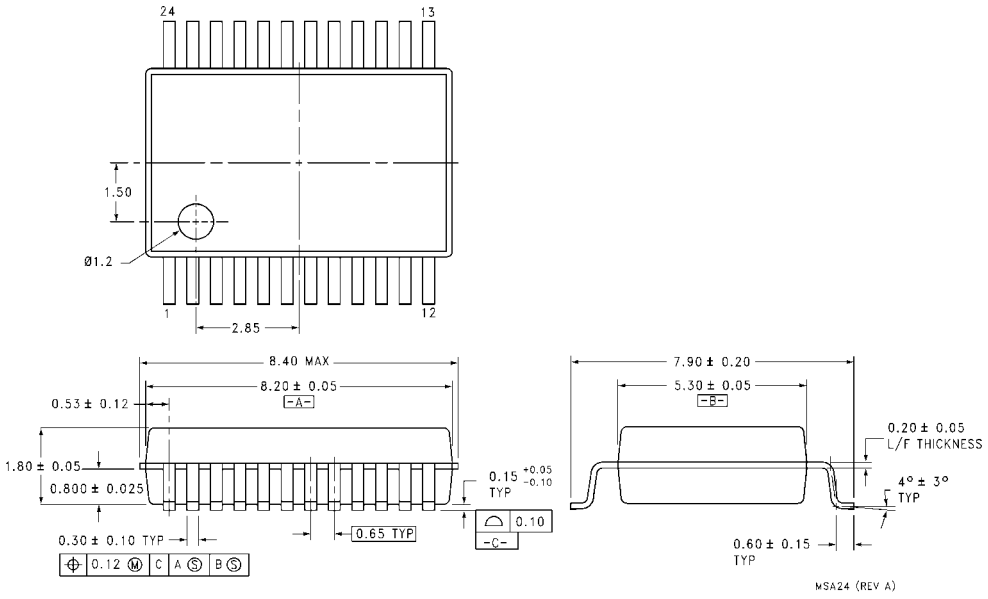
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.0		3.0		ns
$t_S(L)$	$\overline{A}_n$ or $\overline{B}_n$ to $\overline{LEBA}$ or $\overline{LEAB}$	3.0		3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.0		3.0		
$t_H(L)$	$\overline{A}_n$ or $\overline{B}_n$ to $\overline{LEBA}$ or $\overline{LEAB}$	3.0		3.0		3.0		
$t_W(L)$	Latch Enable, B to A Pulse Width, LOW	6.0		9.0		7.5		ns

Physical Dimensions inches (millimeters) unless otherwise noted

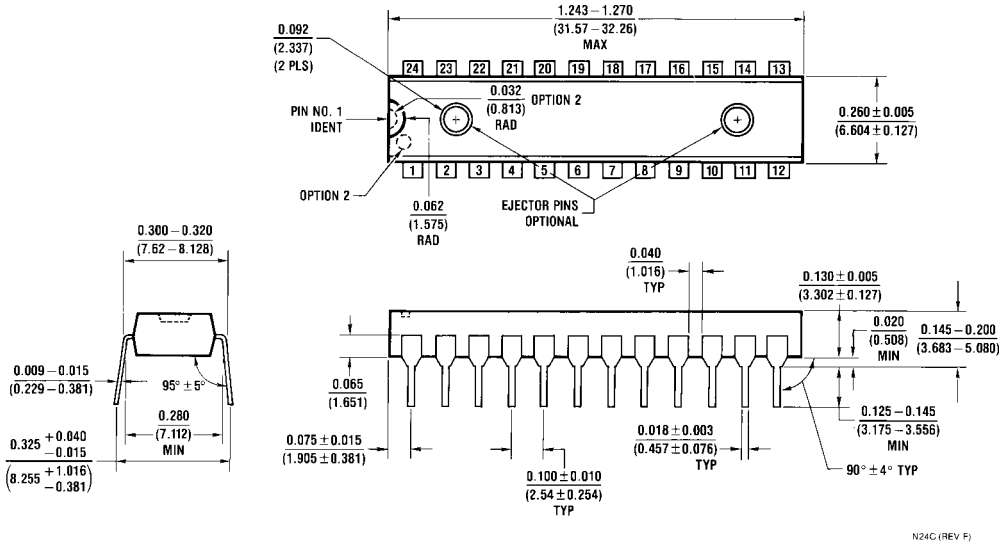


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F545
Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The 74F545 is an 8-bit, 3-STATE, high-speed transceiver. It provides bidirectional drive for bus-oriented microprocessor and digital communications systems. Straight through bidirectional transceivers are featured, with 24 mA bus drive capability on the A Ports and 64 mA bus drive capability on the B Ports.

One input, Transmit/Receive ($T/\overline{R}$) determines the direction of logic signals through the bidirectional transceiver. Transmit enables data from A-to-B Ports; Receive enables data from B-to-A Ports. The Output Enable input disables both A and B Ports by placing them in a 3-STATE condition.

Features

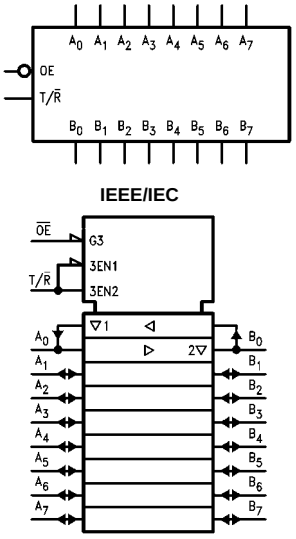
- Higher drive than 8304
- 8-bit bidirectional data flow reduces system package count
- 3-STATE inputs/outputs for interfacing with bus-oriented systems
- 24 mA and 64 mA bus drive capability on A and B Ports, respectively
- Transmit/Receive and Output Enable simplify control logic
- Guaranteed 4000V minimum ESD protection

Ordering Code:

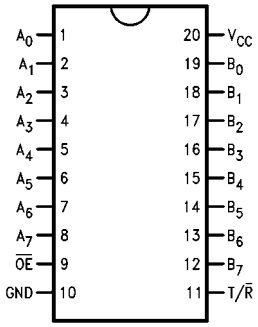
Order Number	Package Number	Package Description
74F545SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F545PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

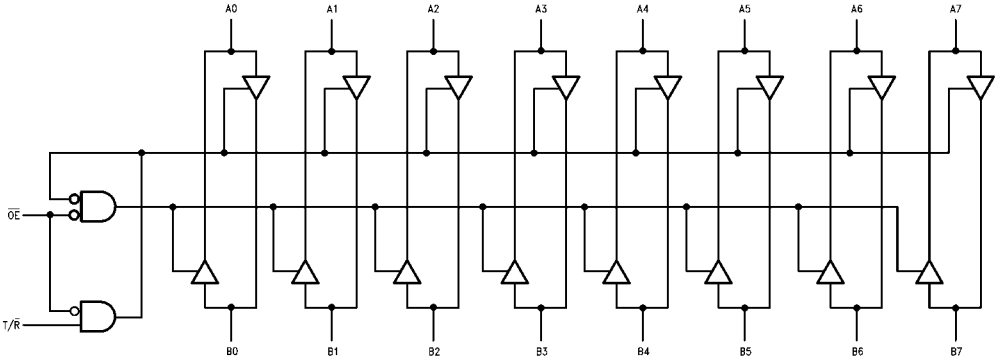
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/2.0	20 µA/–1.2 mA
$T/\overline{R}$	Transmit/Receive Input	1.0/2.0	20 µA/–1.2 mA
A_0–A_7	Side A 3-STATE Inputs or	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)
B_0–B_7	Side B 3-STATE Inputs or	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)

Truth Table

Inputs		Outputs
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

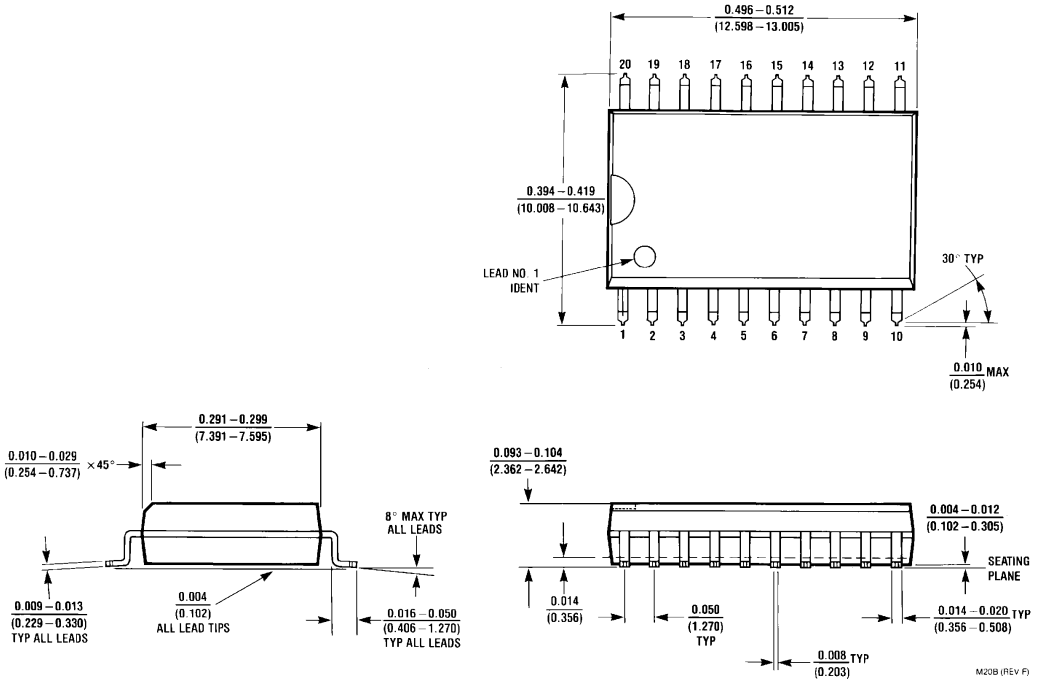
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA ($\overline{OE}$, T/$\overline{R}$)
V_{OH}	Output HIGH	10% V_{CC}	2.5					I_{OH} = −1 mA (A_n)
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA (A_n)
		10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (B_n)
		5% V_{CC}	2.7					I_{OH} = −1 mA (A_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA (A_n)
	Voltage	10% V_{CC}			0.55			I_{OL} = 64 mA (B_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V ($\overline{OE}$, T/$\overline{R}$)
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, T/$\overline{R}$)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.2	mA	Max	V_{IN} = 0.5V ($\overline{OE}$, T/$\overline{R}$)
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V (A_n)
			−100		−225			V_{OUT} = 0V (B_n)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			70	90	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			95	120	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			85	110	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

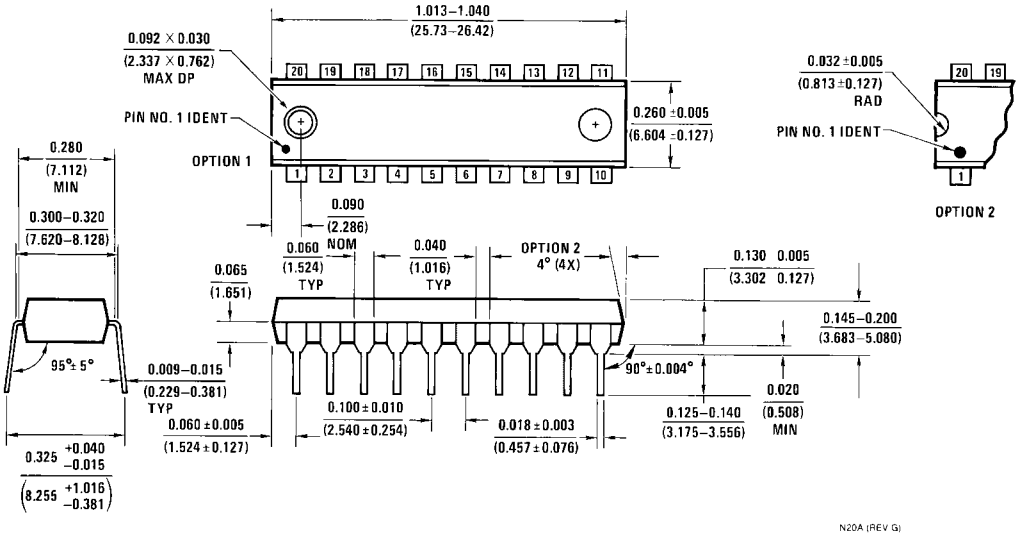
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.2	6.0	2.0	7.5	2.5	7.0	ns
t_{PHL}	A_n to B_n or B_n to A_n	2.5	4.6	6.0	2.0	7.5	2.5	7.0	
t_{PZH}	Output Enable Time	3.0	5.3	7.0	2.5	9.0	3.0	8.0	ns
t_{PZL}		3.5	6.0	8.0	3.0	10.0	3.5	9.0	
t_{PHZ}	Output Disable Time	3.0	5.0	6.5	2.5	9.0	3.0	7.5	
t_{PLZ}		2.0	5.0	6.5	2.0	10.0	2.0	7.5	

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F552
Octal Registered Transceiver with Parity and Flags

General Description

The 74F552 octal transceiver contains two 8-bit registers for temporary storage of data flowing in either direction. Each register has its own clock pulse and clock enable input as well as a flag flip-flop that is set automatically as the register is loaded. The flag output will be reset when the output enable returns to HIGH after reading the output port. Each register has a separate output enable control for its 3-STATE buffer. The separate Clocks, Flags, and Enables provide considerable flexibility as I/O ports for demand-response data transfer. When data is transferred from the A Port to the B Port, a parity bit is generated. On the other hand, when data is transferred from the B Port to the A Port, the parity of input data on B_0–B_7 is checked.

Features

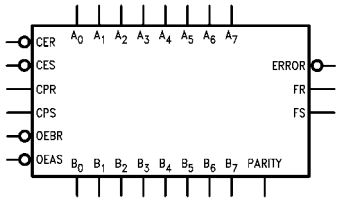
- 8-Bit bidirectional I/O Port with handshake
- Register status flag flip-flops
- Separate clock enable and output enable
- Parity generation and parity check
- B-outputs sink 64 mA
- 3-STATE outputs

Ordering Code:

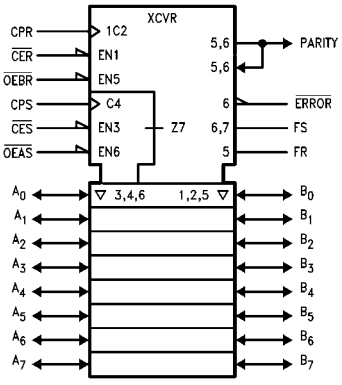
Order Number	Package Number	Package Description
74F552SC	M28B	28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F552QC	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

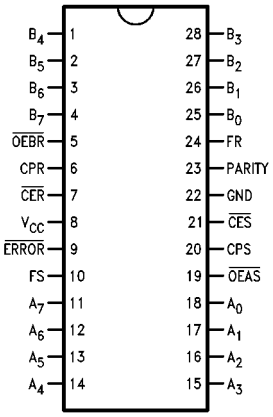
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	A-to-B Port Data Inputs or	3.5/1.083	70 μA/–0.65 mA
	B-to-A 3-STATE	150/40 (33.3)	–3 mA/24 mA (20 mA)
B_0–B_7	B-to-A Transceiver Inputs or	3.5/1.083	70 μA/–0.65 mA
	A-to-B 3-STATE Output	600/106.6 (80)	–12 mA/64 mA (48 mA)
FR	B Port Flag Output	50/33.3	–1 mA/20 mA
FS	A Port Flag Output	50/33.3	–1 mA/20 mA
PARITY	Parity Bit Transceiver Input or Output	3.5/1.083	70 μA/–0.65 mA
		600/106.6 (50)	–12 mA/64 mA (48 mA)
$\overline{\text{ERROR}}$	Parity Check Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{\text{CER}}$	R Registers Clock Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{\text{CES}}$	S Registers Clock Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
CPR	R Registers Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
CPS	S Registers Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{\text{OEBR}}$	B Port and PARITY Output Enable (Active LOW) and Clear FR Input (Active Rising Edge)	1.0/2.0	20 μA/–1.2 mA
$\overline{\text{OEAS}}$	A Port Output Enable (Active LOW) and Clear FS Input (Active Rising Edge)	1.0/2.0	20 μA/–1.2 mA

Functional Description

Data applied to the A-inputs are entered and stored in the R register on the rising edge of the CPR Clock Pulse, provided that the Clock Enable ($\overline{CER}$) is LOW; simultaneously, the status flip-flop is set and the flag (FR) output goes HIGH. As the Clock Enable ($\overline{CER}$) returns to HIGH, the data will be held in the R register. These data entered from the A-inputs will appear at the B Port I/O pins after the Output Enable ($\overline{OEBR}$) has gone LOW. When $\overline{OEBR}$ is LOW, a parity bit appears at the PARITY pin, which will be set HIGH when there is an even number of 1s or all 0s at the Q outputs of the R register. After the data is assimilated, the receiving system clears the flag FR by changing the signal at the $\overline{OEBR}$ pin from LOW-to-HIGH.

Data flow from B-to-A proceeds in the same manner described for A-to-B flow. A LOW at the $\overline{CES}$ pin and a LOW-to-HIGH transition at CPS pin enters the B-input data and the parity-input data into the S registers and the parity register respectively and set the flag output FS to HIGH. A LOW signal at the $\overline{OEAS}$ pin enables the A Port I/O pins and a LOW-to-HIGH transition of the $\overline{OEAS}$ signal clears the FS flag. When $\overline{OEAS}$ is LOW, the parity check output $\overline{ERROR}$ will be HIGH if there is an odd number of 1s at the Q outputs of the S registers and the parity register. The flag FS can be cleared by a LOW-to-HIGH transition of the $\overline{OEAS}$ signal.

Register Function Table

(Applies to R or S Register)

Inputs			Internal	Function
D	CP	$\overline{CE}$	Q	
X	X	H	NC	Hold Data
L	↗	L	L	Load Data
H	↗	L	H	
X	†	L	NC	Keep Old Data

H = HIGH Voltage Level ↗ = LOW-to-HIGH Transition
L = LOW Voltage Level † = Not LOW-to-HIGH Transition
X = Immaterial NC = No Change

Flag Flip-Flop Function Table

(Applies to R or S Flag Flip-Flop)

Inputs			Flag	Function
$\overline{CE}$	CP	$\overline{OE}$	Output	
H	X	†	NC	Hold Flag
L	↗	†	H	Set Flag
X	X	↗	L	Clear Flag

H = HIGH Voltage Level ↗ = LOW-to-HIGH Transition
L = LOW Voltage Level † = Not LOW-to-HIGH Transition
X = Immaterial NC = No Change

Output Control

$\overline{OE}$	Internal Q	A or B Outputs	Function
H	X	Z	Disable Output
L	L	L	Enable Output
L	H	H	Enable Output

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Parity Generation Function

$\overline{OEBR}$	Number of HIGHs in the Q Outputs of the R Register	Parity Output
H	X	Z
L	0, 2, 4, 6, 8	H
L	1, 3, 5, 7	L

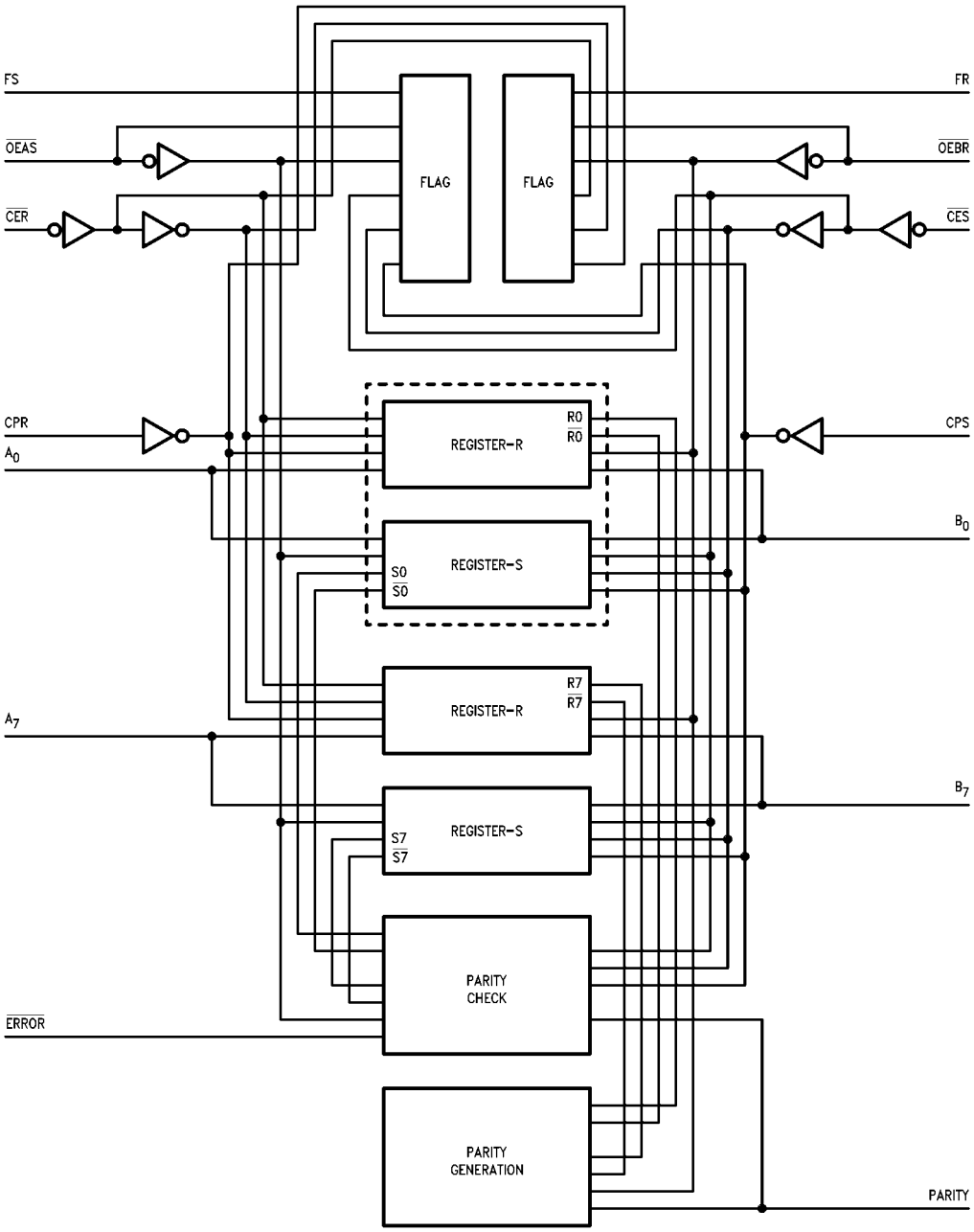
H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Parity Check Function

$\overline{OEAS}$	Number of HIGHs in the Q Outputs of the S Register	Parity Input	$\overline{ERROR}$ Output
H	X	X	H
L	0, 2, 4, 6, 8	L	L
L	1, 3, 5, 7	L	H
L	0, 2, 4, 6, 8	H	H
L	1, 3, 5, 7	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA ($\overline{CER}$, $\overline{CES}$, CPR, CPS, $\overline{OEBR}$, $\overline{OEAS}$)
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA (FR, FS, $\overline{ERROR}$, A_n)
		10% V_{CC}	2.4					I_{OH} = −3 mA (A_n, B_n PARITY)
		10% V_{CC}	2.0					I_{OH} = −15 mA (B_n, PARITY)
		5% V_{CC}	2.7					I_{OH} = −1 mA (FR, FS, $\overline{ERROR}$, A_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n, PARITY)
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA (FR, FS, $\overline{ERROR}$)
		10% V_{CC}			0.5			I_{OL} = 24 mA (A_n)
		10% V_{CC}			0.55			I_{OL} = 64 mA (B_n, PARITY)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V ($\overline{CER}$, $\overline{CES}$, CPR, CPS, $\overline{OEBR}$, $\overline{OEAS}$)
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V ($\overline{CER}$, $\overline{CES}$, CPR, CPS, $\overline{OEBR}$, $\overline{OEAS}$)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n, PARITY)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC} (FR, FS, $\overline{ERROR}$, A_n, B_n, PARITY)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V ($\overline{CER}$, $\overline{CES}$, CPR, CPS)
					−1.2			V_{IN} = 0.5V ($\overline{OEBR}$, $\overline{OEAS}$)
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (A_n, B_n, PARITY)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n, PARITY)
I_{OS}	Output Short-Circuit Current		−60		−175	mA	Max	V_{OUT} = 0V (FR, FS, $\overline{ERROR}$, A_n)
			−100		−250			V_{OUT} = 0V (B_n, PARITY)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V (A_n, B_n, PARITY)
I_{CCH}	Power Supply Current			100	150	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			100	150	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			110	165	mA	Max	V_O = HIGH Z

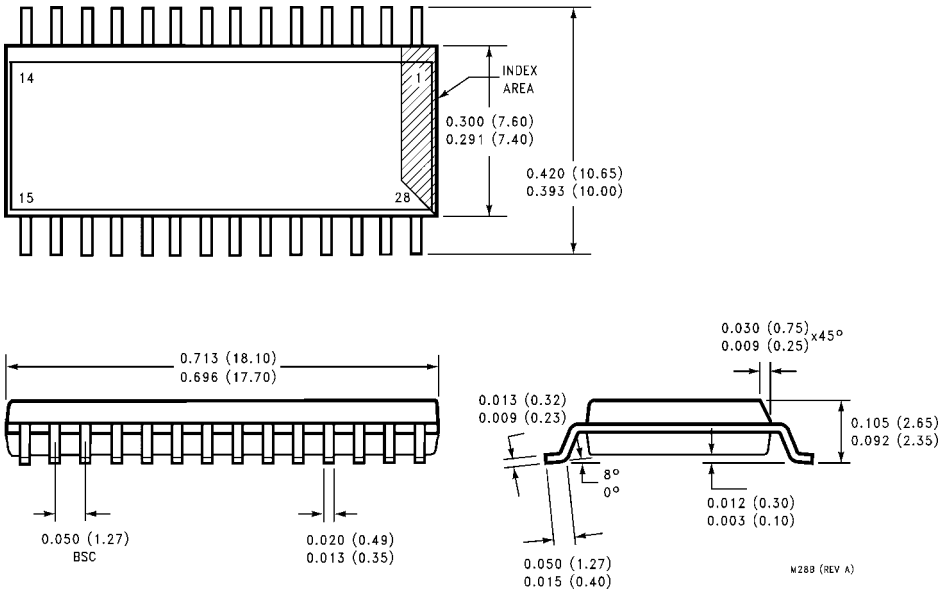
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.5	6.0	8.0	3.0	9.0	ns
t_{PHL}	CPS or CPR to A_n or B_n	4.0	7.0	9.5	3.5	10.5	
t_{PLH}	Propagation Delay CPS or CPR to FS or FR	3.0	5.5	7.5	2.5	8.5	ns
t_{PHL}	Propagation Delay $\overline{OEAS}$ to FS	3.5	6.0	8.0	3.0	9.0	ns
t_{PLH}	Propagation Delay	8.0	14.0	18.0	7.0	20.0	ns
t_{PHL}	CPR to Parity	8.5	14.5	18.5	7.5	20.5	
t_{PLH}	Propagation Delay	8.0	13.5	17.5	7.0	19.5	ns
t_{PHL}	CPS to $\overline{ERROR}$	7.5	13.0	16.5	6.5	18.5	
t_{PLH}	Propagation Delay	3.5	6.0	8.0	3.0	9.0	ns
t_{PHL}	$\overline{OEAS}$ to $\overline{ERROR}$	3.0	5.0	7.0	2.5	8.0	
t_{PZH}	Enable Time $\overline{OEAS}$	3.0	5.5	7.5	2.5	8.5	ns
t_{PZL}	or $\overline{OEBR}$ to B_n or A_n	3.5	7.0	9.5	3.0	10.5	
t_{PHZ}	Disable Time $\overline{OEAS}$	3.0	6.5	8.5	2.5	9.5	
t_{PLZ}	or $\overline{OEBR}$ to B_n or A_n	3.0	5.5	7.5	2.5	8.5	
t_{PZH}	Enable Time	3.0	4.5	7.5	2.5	8.5	ns
t_{PZL}	$\overline{OEBR}$ to Parity	3.5	6.0	9.5	3.0	10.5	
t_{PHZ}	Disable Time	3.0	5.5	8.5	2.5	9.5	
t_{PLZ}	$\overline{OEBR}$ to Parity	3.0	6.5	7.5	2.5	8.5	

AC Operating Requirements

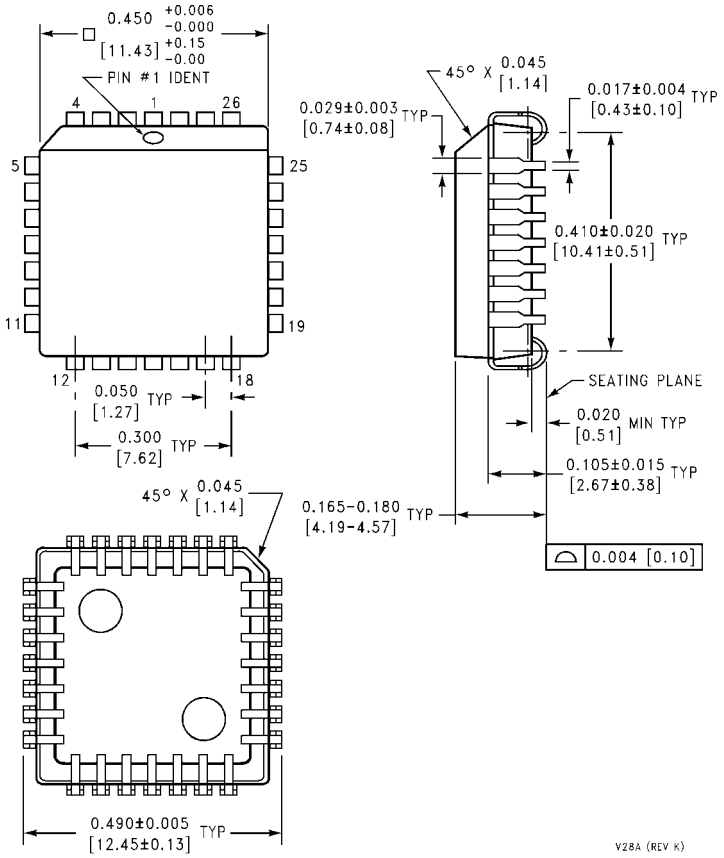
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	7.5		8.5		ns
$t_S(L)$	A_n or B_n or Parity to CPS or CPR	4.5		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	A_n or B_n or Parity to CPS or CPR	0		0		
$t_S(H)$	Setup, Time HIGH or LOW	6.0		7.0		ns
$t_S(L)$	$\overline{CES}$ or $\overline{CER}$ to CPS or CPR	10.0		11.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	$\overline{CES}$ or $\overline{CER}$ to CPS or CPR	0		0		
$t_W(H)$	Pulse Width, HIGH or LOW	4.0		4.5		ns
$t_W(L)$	CPS or CPR	6.0		7.0		

Physical Dimensions inches (millimeters) unless otherwise noted



28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M28B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
Package Number V28A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F563
Octal D-Type Latch with 3-STATE Outputs

General Description

The 74F563 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

This device is functionally identical to the 74F573, but has inverted outputs.

Features

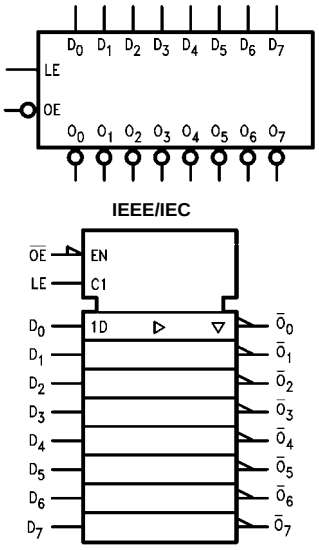
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 74F573

Ordering Code:

Order Number	Package Number	Package Description
74F563SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F563SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F563PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

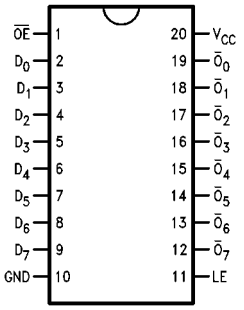
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
LE	Latch Enable Input (Active HIGH)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{O}_0$–$\overline{O}_7$	3-STATE Latch Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

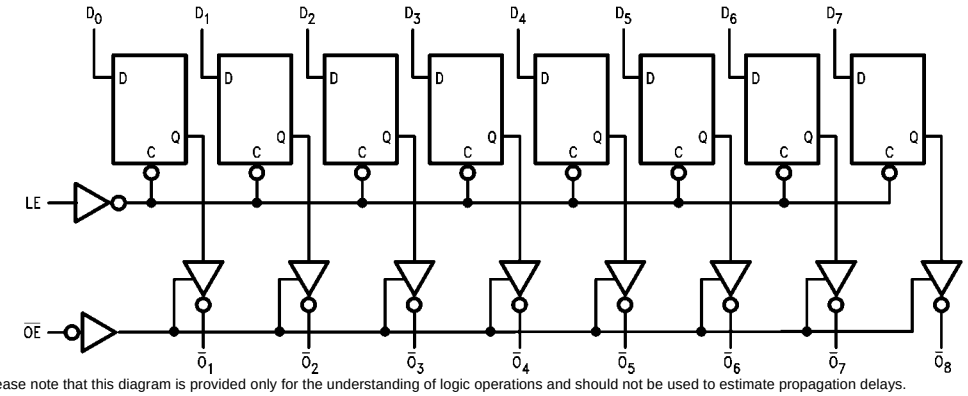
The 74F563 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Function Table

Inputs			Internal	Output	Function
$\overline{OE}$	LE	D	Q	O	
H	X	X	X	Z	High Z
H	H	L	H	Z	High Z
H	H	H	L	Z	High Z
H	L	X	NC	Z	Latched
L	H	L	H	H	Transparent
L	H	H	L	L	Transparent
L	L	X	NC	NC	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCL}	Power Supply Current			40	61	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			40	61	mA	Max	V_O = HIGH Z

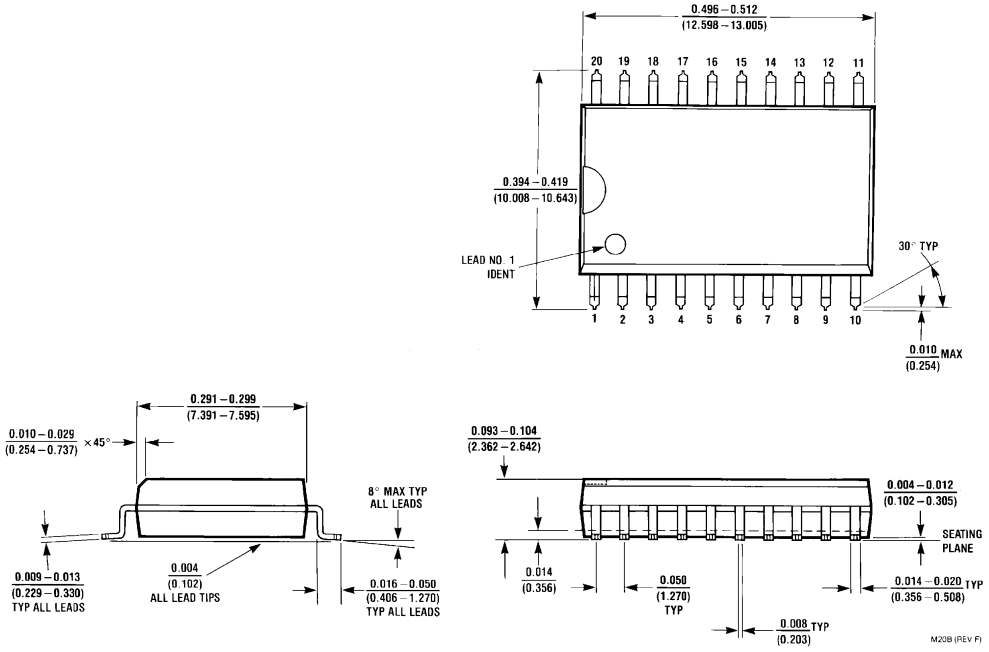
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.5		8.5	3.0	10.5	3.0	9.5	ns
t_{PHL}	D_n to $\overline{O}_n$	2.5		6.5	2.0	7.5	2.0	7.0	
t_{PLH}	Propagation Delay	4.5		9.5	4.0	11.0	4.0	10.5	ns
t_{PHL}	LE to $\overline{O}_n$	3.0		7.0	2.5	7.5	2.5	7.0	
t_{PZH}	Output Enable Time	2.0		7.5	2.0	9.5	2.0	9.0	ns
t_{PZL}		3.0		8.5	2.5	10.0	1.5	9.5	
t_{PHZ}	Output Disable Time	1.5		5.5	1.5	7.0	1.5	6.5	
t_{PLZ}		1.5		5.5	1.5	5.5	1.5	5.5	

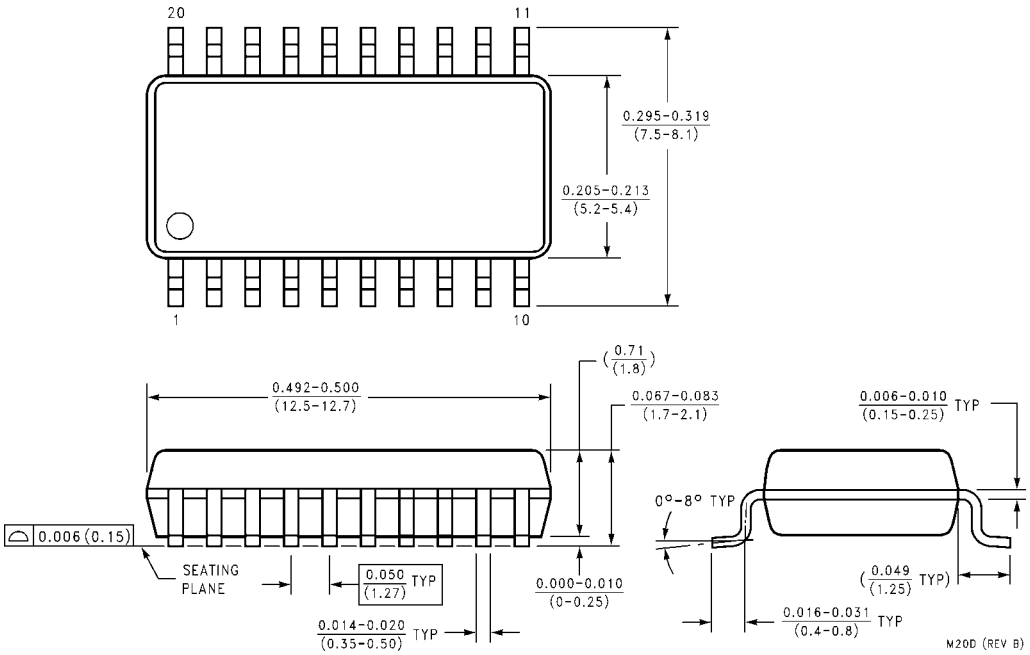
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_S(L)$	D_n to LE	2.0		2.0		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.0		3.0		ns
$t_H(L)$	D_n to LE	3.0		3.0		3.0		
$t_W(H)$	LE Pulse Width, HIGH	4.0		4.0		4.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

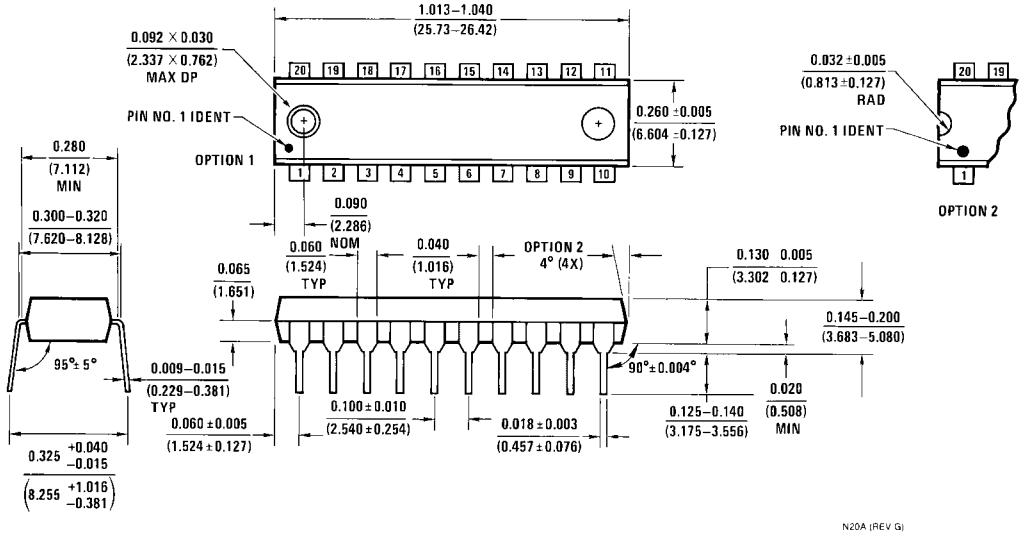


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1983
Revised August 1999

74F564
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The 74F564 is a high-speed, low power octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable ($\overline{OE}$). The information presented to the D inputs is sorted in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

This device is functionally identical to the 74F574, but has inverted outputs.

Features

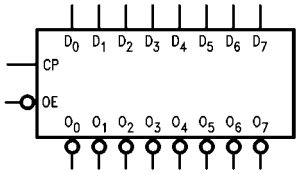
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 74F574
- 3-STATE outputs for bus-oriented applications

Ordering Code:

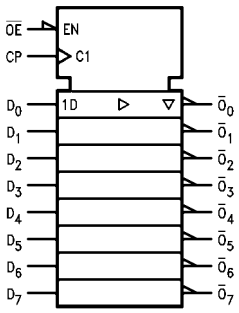
Order Number	Package Number	Package Description
74F564SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F564PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

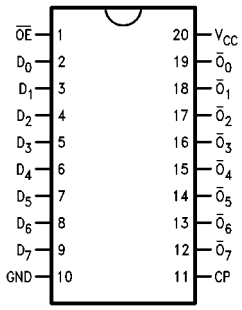
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 µA/–0.6 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{O}_0$–$\overline{O}_7$	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

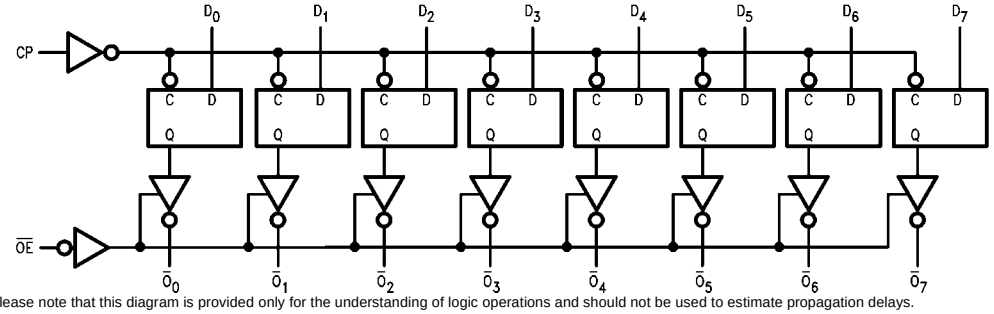
The 74F564 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	⌐	L	H	Z	Load
H	⌐	H	L	Z	Load
L	⌐	L	H	H	Data Available
L	⌐	H	L	L	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			55	86	mA	Max	V_O = HIGH Z

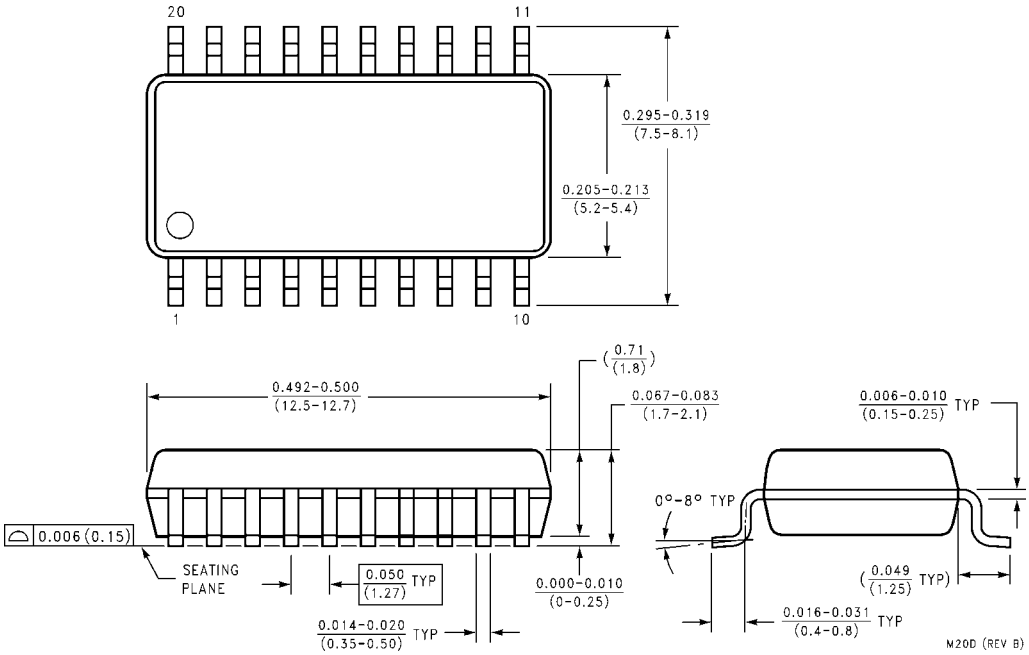
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100			70		MHz
t_{PLH}	Propagation Delay	2.5	5.2	8.5	2.5	8.5	ns
t_{PHL}	CP to $\overline{O}_n$	2.5	5.9	8.5	2.5	8.5	
t_{PZH}	Output Enable Time	3.0	5.6	9.0	2.5	10.0	ns
t_{PZL}		3.0	6.2	9.0	2.5	10.0	
t_{PHZ}	Output Disable Time	1.5	3.4	5.5	1.5	6.5	
t_{PLZ}		1.5	2.7	5.5	1.5	6.5	

AC Operating Requirements

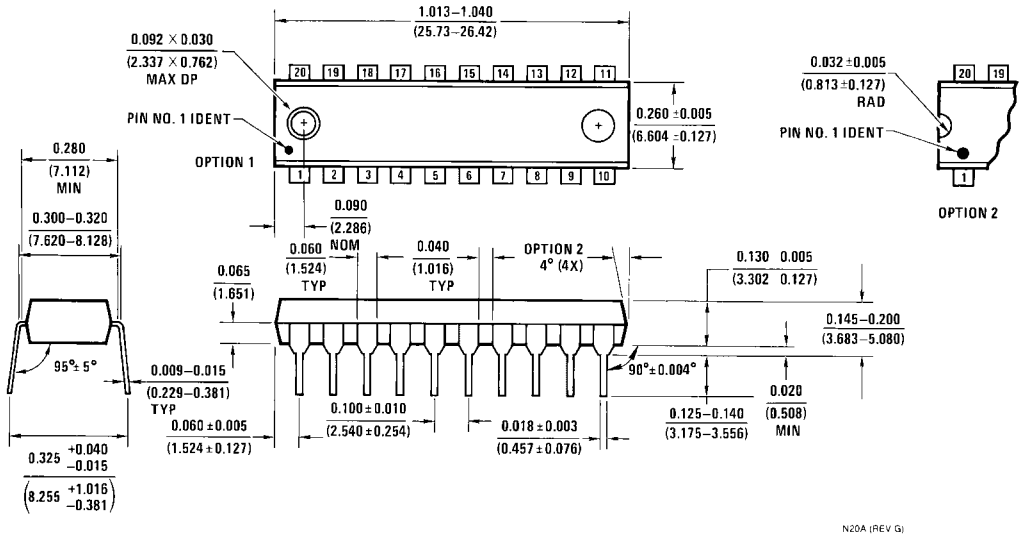
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		ns
$t_S(L)$	D_n to CP	2.5		2.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		
$t_H(L)$	D_n to CP	2.0		2.0		
$t_W(H)$	CP Pulse Width	5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F569
4-Bit Bidirectional Counter with 3-STATE Outputs

General Description

The 74F569 is a fully synchronous, reversible counter with 3-STATE outputs. The 74F569 is a binary counter, featuring preset capability for programmable operation, carry lookahead for easy cascading, and a U/$\overline{D}$ input to control the direction of counting. For maximum flexibility there are both synchronous and master asynchronous reset inputs as well as both Clocked Carry ($\overline{CC}$) and Terminal Count ($\overline{TC}$) outputs. All state changes except Master Reset are initiated by the rising edge of the clock. A HIGH signal on the Output Enable ($\overline{OE}$) input forces the output buffers into the high impedance state but does not prevent counting, resetting or parallel loading.

Features

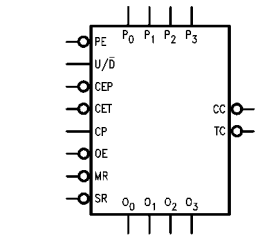
- Synchronous counting and loading
- Lookahead carry capability for easy cascading
- Preset capability for programmable operation
- 3-STATE outputs for bus organized systems

Ordering Code:

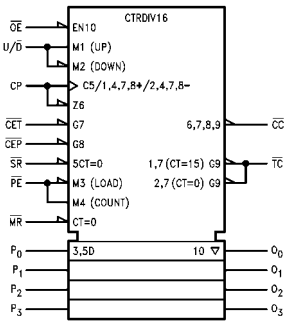
Order Number	Package Number	Package Description
74F569SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F569SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F569PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

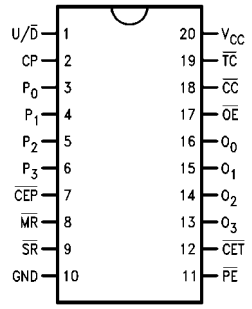
Logic Symbols



IEEE/IEC



Connection Diagram



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Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
P_0–P_3	Parallel Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{CEP}$	Count Enable Parallel Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{CET}$	Count Enable Trickle Input (Active LOW)	1.0/1.0	20 μA/–1.2 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{PE}$	Parallel Enable Input (Active LOW)	1.0/1.0	20 μA/–1.2 mA
U/$\overline{D}$	Up/Down Count Control Input	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{MR}$	Master Reset Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{SR}$	Synchronous Reset Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
O_0–O_3	3-STATE Parallel Data Outputs	150/40(33.3)	–3 mA/24 mA (20 mA)
$\overline{TC}$	Terminal Count Output (Active LOW)	50/33.3	–1 mA/20 mA
$\overline{CC}$	Clocked Carry Output (Active LOW)	50/33.3	–1 mA/20 mA

Functional Description

The 74F569 counts in the modulo-16 binary sequence. From state 15 it will increment to state 0 in the Up mode; in the Down mode it will decrement from 0 to 15. The clock inputs of all flip-flops are driven in parallel through a clock buffer. All state changes (except due to Master Reset) occurs synchronously with the LOW-to-HIGH transition of the Clock Pulse (CP) input signal.

The circuits have five fundamental modes of operation, in order of precedence: asynchronous reset, synchronous reset, parallel load, count and hold. Five control inputs—Master Reset ($\overline{MR}$), Synchronous Reset ($\overline{SR}$), Parallel Enable ($\overline{PE}$), Count Enable Parallel ($\overline{CEP}$) and Count Enable Trickle $\overline{CET}$)—plus the Up/Down (U/$\overline{D}$) input, determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides all other inputs and asynchronously forces the flip-flop Q outputs LOW. A LOW signal on $\overline{SR}$ overrides counting and parallel loading and allows the Q outputs to go LOW on the next rising edge of CP. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{MR}$, $\overline{SR}$ and $\overline{PE}$ HIGH, $\overline{CEP}$ and $\overline{CET}$ permit counting when both are LOW. Conversely, a HIGH signal on either $\overline{CEP}$ or $\overline{CET}$ inhibits counting.

The 74F569 uses edge-triggered flip-flops and changing the $\overline{SR}$, $\overline{PE}$, $\overline{CEP}$, $\overline{CET}$ or U/$\overline{D}$ inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

Two types of outputs are provided as overflow/underflow indicators. The Terminal Count ($\overline{TC}$) output is normally HIGH and goes LOW providing $\overline{CET}$ is LOW, when the counter reaches zero in the Down mode, or reaches maximum

(15) in the Up mode. $\overline{TC}$ will then remain LOW until a state change occurs, whether by counting or presetting, or until U/$\overline{D}$ or $\overline{CET}$ is changed. To implement synchronous multistage counters, the connections between the $\overline{TC}$ output and the $\overline{CEP}$ and $\overline{CET}$ inputs can provide either slow or fast carry propagation.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to $\overline{TC}$ delay of the first stage, plus the cumulative $\overline{CET}$ to $\overline{TC}$ delays of the intermediate stages, plus the $\overline{CET}$ to CP setup time of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in Figure 2 are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle takes 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to $\overline{TC}$ delay of the first stage plus the $\overline{CEP}$ to CP setup time of the last stage. The $\overline{TC}$ output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters. For such applications, the Clocked Carry ($\overline{CC}$) output is provided. The $\overline{CC}$ output is normally HIGH. When $\overline{CEP}$, $\overline{CET}$, and $\overline{TC}$ are LOW, the $\overline{CC}$ output will go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again, as shown in the $\overline{CC}$ Truth Table. When the Output Enable ($\overline{OE}$) is LOW, the parallel data outputs O_0–O_3 are active and follow the flip-flop Q outputs. A HIGH signal on $\overline{OE}$ forces O_0–O_3 to the High Z state but does not prevent counting, loading or resetting.

Logic Equations

Count Enable = $\overline{CEP} \cdot \overline{CET} \cdot PE$

Up: $\overline{TC} = Q_0 \cdot Q_1 \cdot Q_2 \cdot Q_3 \cdot (Up) \cdot \overline{CET}$

Down: $\overline{TC} = \overline{Q}_0 \cdot \overline{Q}_1 \cdot \overline{Q}_2 \cdot \overline{Q}_3 \cdot (Down) \cdot \overline{CET}$

$\overline{CC}$ Truth Table

Inputs						Output
$\overline{SR}$	$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	$\overline{TC}$ (Note 1)	CP	$\overline{CC}$
L	X	X	X	X	X	H
X	L	X	X	X	X	H
X	X	H	X	X	X	H
X	X	X	H	X	X	H
X	X	X	X	H	X	H
H	H	L	L	L	⌐⌐	⌐⌐

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level ⌐⌐ = HIGH-to-LOW-to-HIGH Clock Transition

Note 1: $\overline{TC}$ is generated internally

Mode Select Table

Inputs						Operating Mode
$\overline{MR}$	$\overline{SR}$	$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	U/$\overline{D}$	
L	X	X	X	X	X	Asynchronous Reset
H	L	X	X	X	X	Synchronous Reset
H	H	L	X	X	X	Parallel Load
H	H	H	H	X	X	Hold
H	H	H	X	H	X	Hold
H	H	H	L	L	H	Count Up
H	H	H	L	L	L	Count Down

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

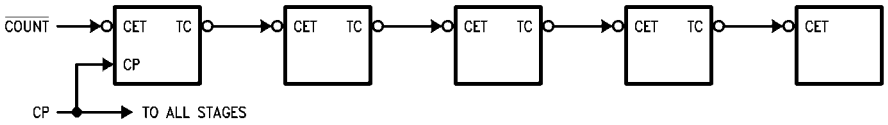


FIGURE 1. Multistage Counter with Ripple Carry

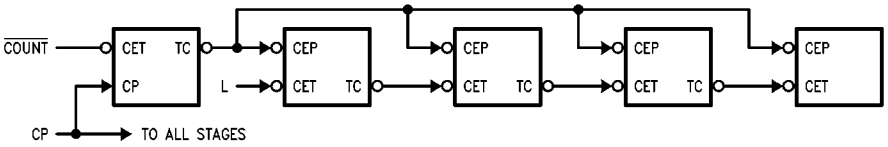
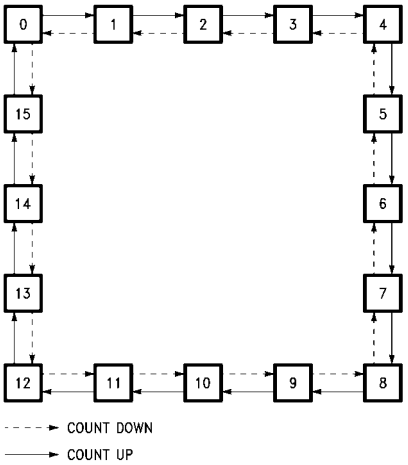
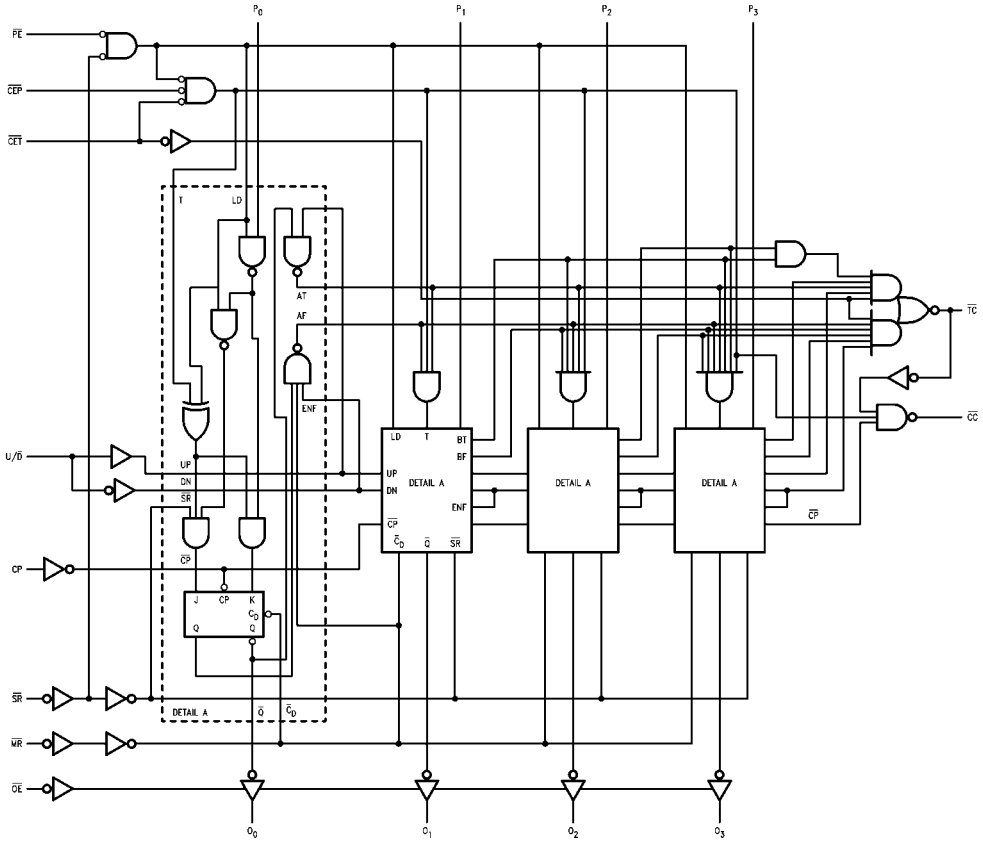


FIGURE 2. Multistage Counter with Lookahead Carry

State Diagram



Logic Diagram



Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA ($\overline{TC}$, $\overline{CC}$, O_n)
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA (O_n)
		5% V_{CC}	2.7					I_{OH} = −1 mA ($\overline{TC}$, $\overline{CC}$, O_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (O_n)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA ($\overline{TC}$, $\overline{CC}$)
	Voltage	10% V_{CC}			0.5			I_{OL} = 24 mA (O_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC} ($\overline{TC}$, $\overline{CC}$, O_n)
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (P_n, $\overline{CEP}$, CP, U/$\overline{D}$, $\overline{OE}$, $\overline{MR}$, $\overline{SR}$)
					−1.2	mA	Max	V_{IN} = 0.5V ($\overline{PE}$, $\overline{CET}$)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V (O_n)
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V (O_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V ($\overline{TC}$, $\overline{CC}$, O_n)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V (O_n)
I_{CCH}	Power Supply Current			45	67	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			45	67	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			45	67	mA	Max	V_O = HIGH Z

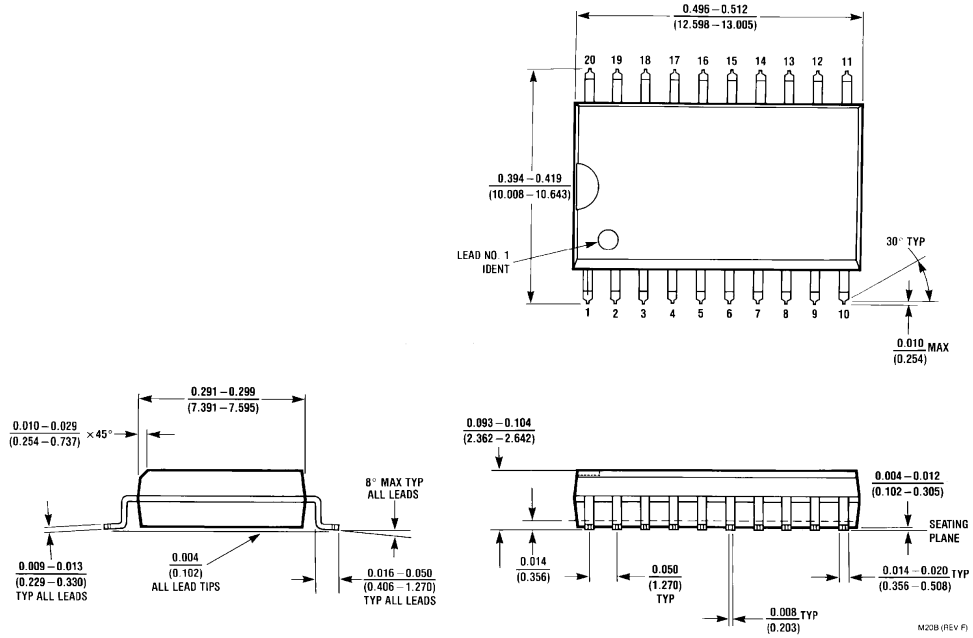
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	90			70		MHz
t_{PLH}	Propagation Delay	3.0	6.5	8.5	3.0	9.5	ns
t_{PHL}	CP to O_n ($\overline{PE}$ HIGH or LOW)	4.0	9.0	11.5	4.0	13.0	
t_{PLH}	Propagation Delay	5.5	12.0	15.5	5.5	17.5	ns
t_{PHL}	CP to $\overline{TC}$	4.0	8.5	12.5	4.0	13.0	
t_{PLH}	Propagation Delay	2.5	4.5	6.5	2.5	7.0	ns
t_{PHL}	$\overline{CET}$ to $\overline{TC}$	2.5	6.0	11.0	2.5	12.0	
t_{PLH}	Propagation Delay	3.5	8.5	11.5	3.5	12.5	ns
t_{PHL}	U/$\overline{D}$ to $\overline{TC}$	4.0	8.0	12.0	4.0	13.0	
t_{PLH}	Propagation Delay	2.5	5.5	7.0	2.0	8.0	ns
t_{PHL}	CP to $\overline{CC}$	2.0	4.5	6.0	2.0	7.0	
t_{PLH}	Propagation Delay	2.5	5.0	6.5	2.0	7.5	ns
t_{PHL}	$\overline{CEP}$, $\overline{CET}$ to $\overline{CC}$	4.0	8.5	11.0	4.0	12.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to O_n	5.0	10.0	13.0	5.0	14.5	ns
t_{PZH}	Output Enable Time	2.5	5.5	8.0	2.5	8.5	ns
t_{PZL}	$\overline{OE}$ to O_n	3.0	6.0	9.0	3.0	10.0	
t_{PHZ}	Output Disable Time	1.5	5.0	7.0	1.5	8.0	
t_{PLZ}	$\overline{OE}$ to O_n	2.0	4.5	6.0	2.0	7.0	

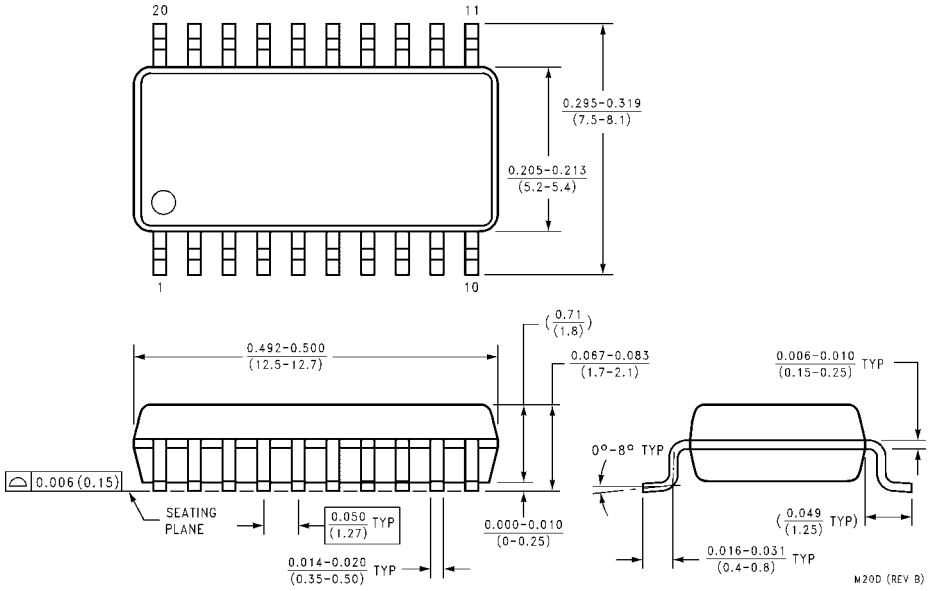
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		4.5		ns
$t_S(L)$	P_n to CP	4.0		4.5		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.5		ns
$t_H(L)$	P_n to CP	3.0		3.5		
$t_S(H)$	Setup Time, HIGH or LOW	7.0		8.0		ns
$t_S(L)$	$\overline{CEP}$ or $\overline{CET}$ to CP	5.0		6.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		ns
$t_H(L)$	$\overline{CEP}$ or $\overline{CET}$ to CP	0.5		0.5		
$t_S(H)$	Setup Time, HIGH or LOW	8.0		9.0		ns
$t_S(L)$	$\overline{PE}$ to CP	8.0		9.0		
$t_H(H)$	Hold Time, HIGH or LOW	0.0		1.0		ns
$t_H(L)$	$\overline{PE}$ to CP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	11.0		12.5		ns
$t_S(L)$	U/$\overline{D}$ to CP	7.0		8.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		ns
$t_H(L)$	U/$\overline{D}$ to CP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	10.5		11.0		ns
$t_S(L)$	$\overline{SR}$ to CP	8.5		9.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		ns
$t_H(L)$	$\overline{SR}$ to CP	0		0		
$t_W(H)$	CP Pulse Width,	4.0		4.5		ns
$t_W(L)$	HIGH or LOW	7.0		8.0		
$t_W(L)$	$\overline{MR}$ Pulse Width, LOW	4.5		6.0		ns
t_{REC}	$\overline{MR}$ Recovery Time	6.0		8.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

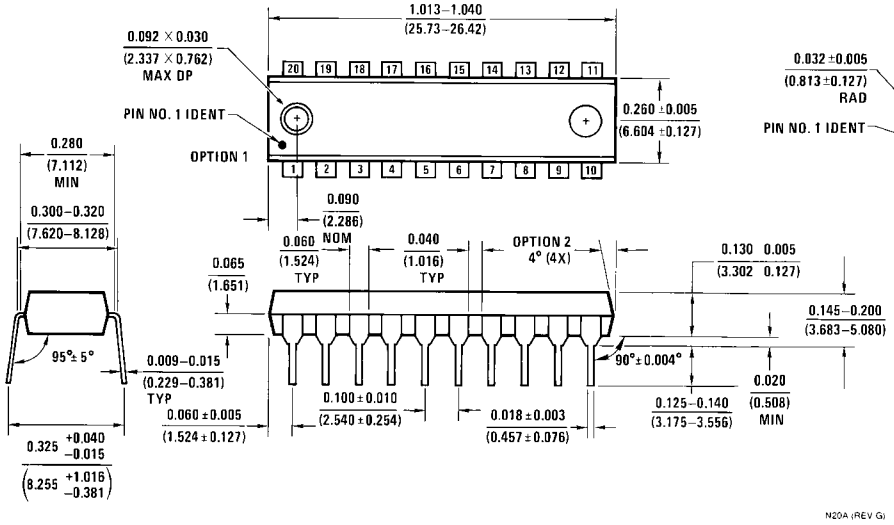


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F573
Octal D-Type Latch with 3-STATE Outputs

General Description

The 74F573 is a high speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

This device is functionally identical to the 74F373 but has different pinouts.

Features

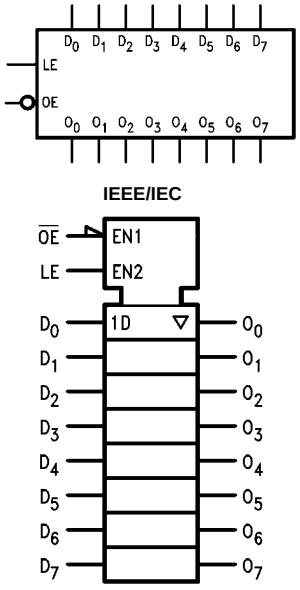
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 74F373
- 3-STATE outputs for bus interfacing
- Guaranteed 4000V minimum ESD protection

Ordering Code:

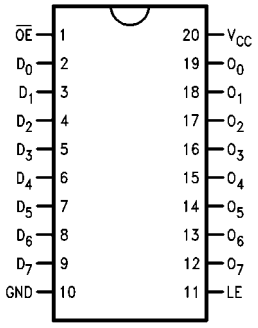
Order Number	Package Number	Package Description
74F573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F573PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
LE	Latch Enable Input (Active HIGH)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
O_0–O_7	3-STATE Latch Outputs	150/40(33.3)	–3 mA/24 mA (20 mA)

Functional Description

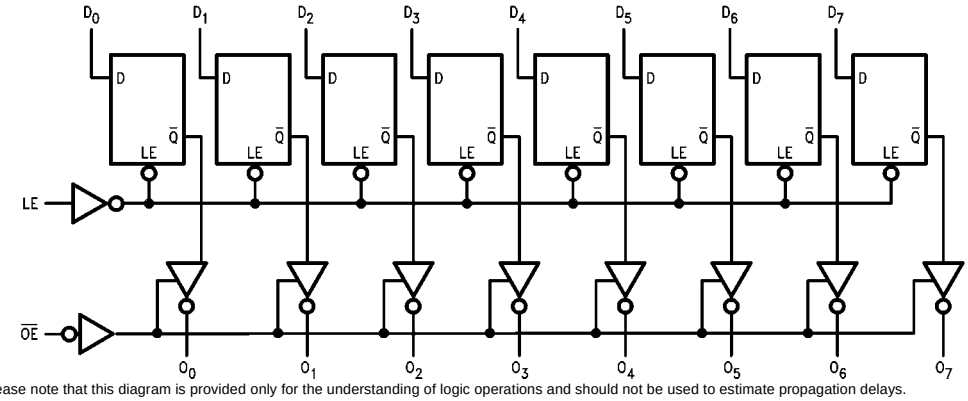
The 74F573 contains eight D-type latches with 3-state output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-state buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Function Table

Inputs			Outputs
$\overline{OE}$	LE	D	O
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
O_0 = Value stored from previous clock cycle

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				20.0 5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCL}	Power Supply Current			35	55	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			35	55	mA	Max	V_O = HIGH Z

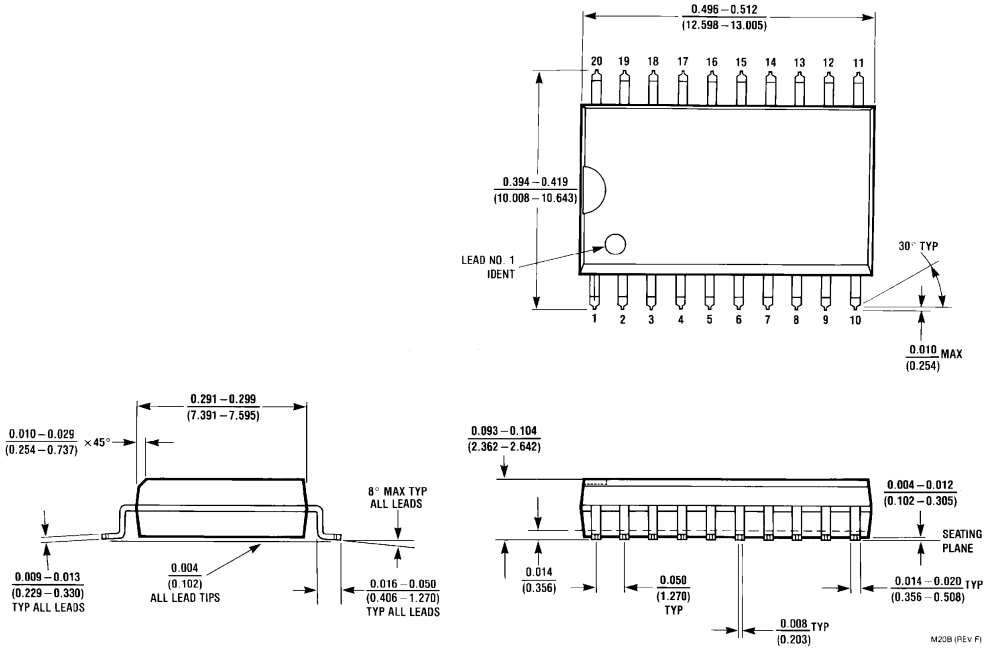
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	5.3	7.0	3.0	9.0	3.0	8.0	ns
t_{PHL}	D_n to O_n	2.0	3.7	6.0	2.0	7.0	2.0	6.5	
t_{PLH}	Propagation Delay	5.0	9.0	11.0	5.0	13.5	5.0	12.0	ns
t_{PHL}	LE to O_n	3.0	5.2	7.0	3.0	7.5	3.0	7.0	
t_{PZH}	Output Enable Time	2.0	5.0	8.0	2.0	10.0	2.0	9.0	ns
t_{PZL}		2.0	5.6	8.5	2.0	10.0	2.0	9.5	
t_{PHZ}	Output Disable Time	1.5	4.5	5.5	1.5	7.0	1.5	6.5	
t_{PLZ}		1.5	3.8	5.5	1.5	5.5	1.5	5.5	

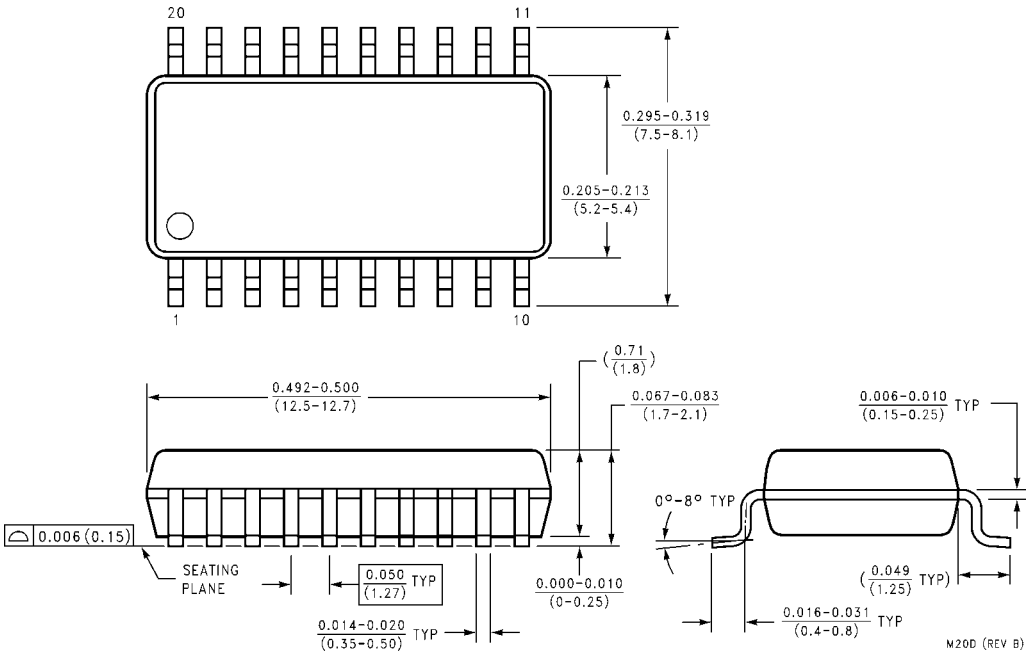
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_S(L)$	D_n to LE	2.0		2.0		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.0		3.0		ns
$t_H(L)$	D_n to LE	3.5		4.0		3.5		
$t_W(H)$	LE Pulse Width, HIGH	4.0		4.0		4.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

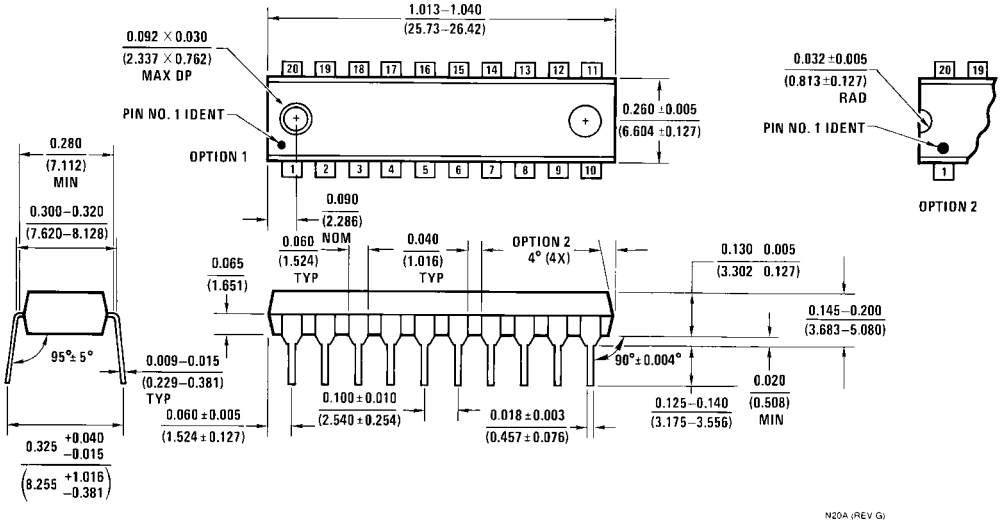


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F574
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The 74F574 is a high-speed, low power octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable ($\overline{OE}$). The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

This device is functionally identical to the 74F374 except for the pinouts.

Features

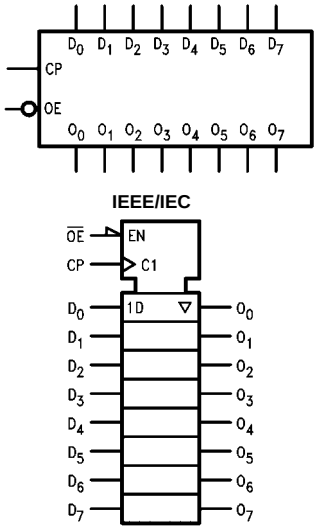
- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 74F374
- 3-STATE outputs for bus-oriented applications

Ordering Code:

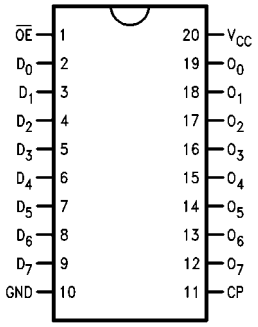
Order Number	Package Number	Package Description
74F574SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F574PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 μA/–0.6 mA
CP	Clock Pulse Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{OE}$	3-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
O_0–O_7	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

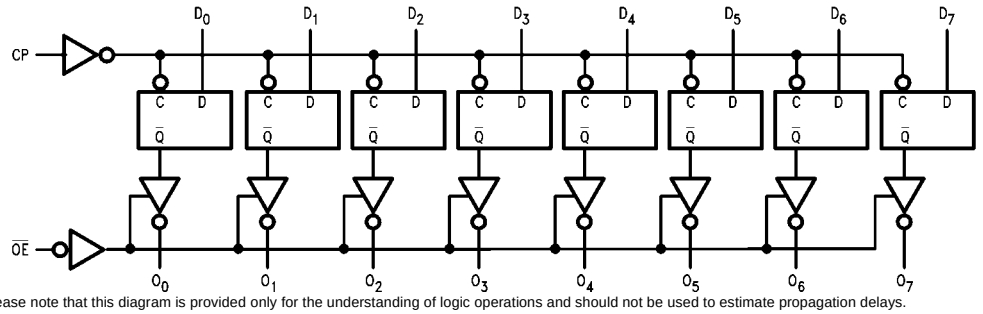
The 74F574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	⌐	L	L	Z	Load
H	⌐	H	H	Z	Load
L	⌐	L	L	L	Data Available
L	⌐	H	H	H	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			55	86	mA	Max	V_O = HIGH Z

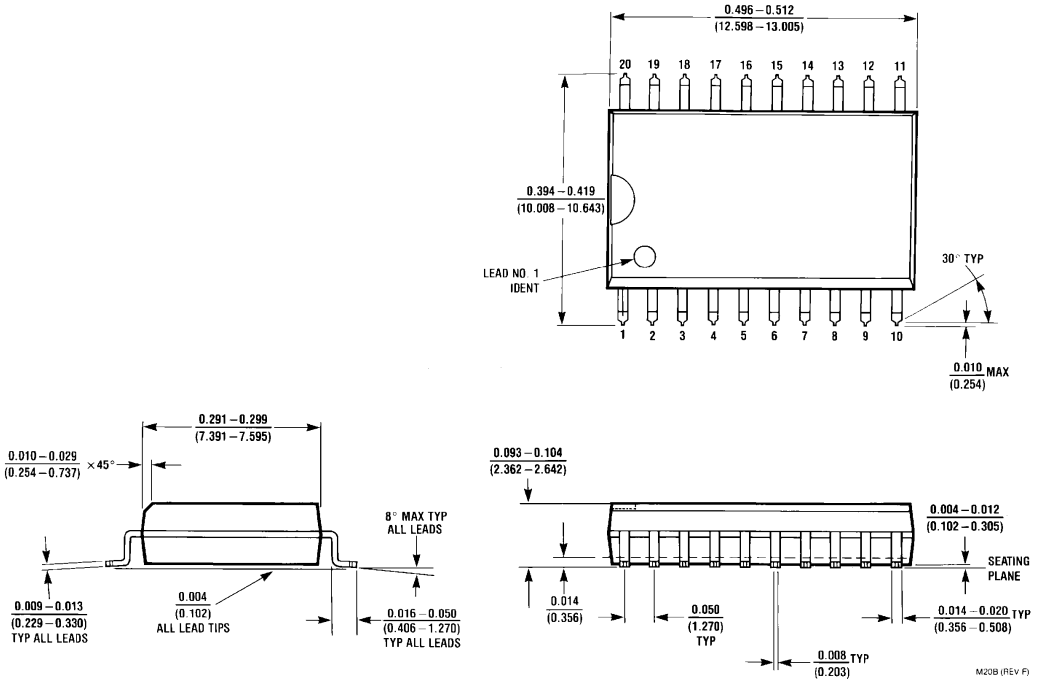
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100			60		70		MHz
t_{PLH}	Propagation Delay	2.5	5.3	8.5	2.5	9.5	2.5	8.5	ns
t_{PHL}	CP to O_n	2.5	5.3	8.5	2.5	9.5	2.5	8.5	
t_{PZH}	Output Enable Time	3.0	5.5	9.0	2.5	10.5	2.5	10.0	ns
t_{PZL}		3.0	6.0	9.0	2.5	10.5	2.5	10.0	
t_{PHZ}	Output Disable Time	1.5	3.3	5.5	1.5	7.0	1.5	6.5	ns
t_{PLZ}		1.5	2.8	5.5	1.5	7.0	1.5	6.5	

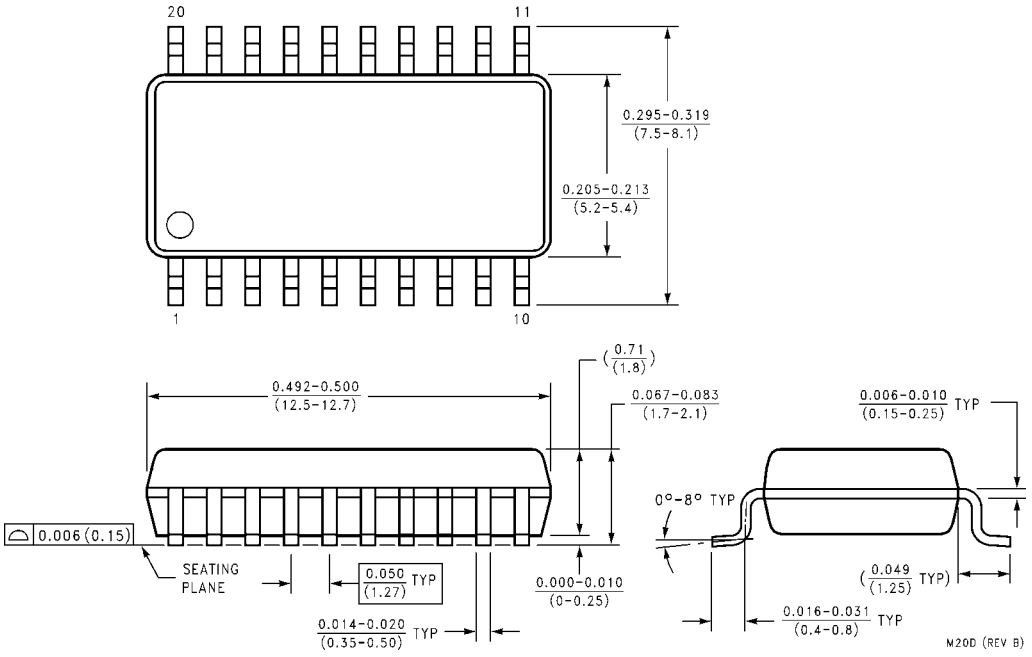
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Set-up Time, HIGH or LOW	2.5		3.0		2.5		ns
$t_S(L)$	D_n to CP	2.0		2.5		2.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		ns
$t_H(L)$	D_n to CP	2.0		2.0		2.0		
$t_W(H)$	CP Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted

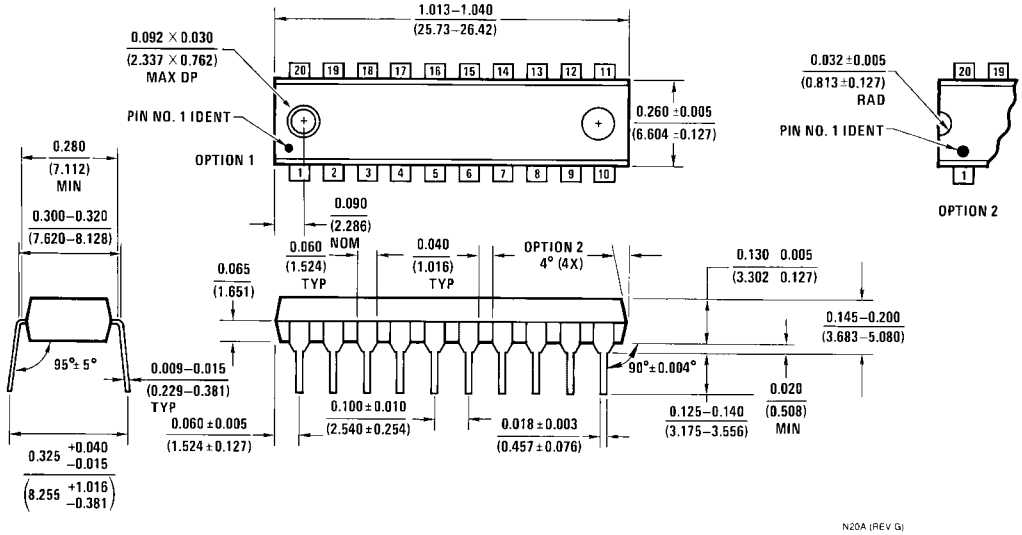


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F579
8-Bit Bidirectional Binary Counter with 3-STATE Outputs

General Description

The 74F579 is a fully synchronous 8-stage up/down counter with multiplexed 3-STATE I/O ports for bus-oriented applications. It features a preset capability for programmable operation, carry lookahead for easy cascading and a U/$\overline{D}$ input to control the direction of counting. All state changes, whether in counting or parallel loading, are initiated by the rising edge of the clock.

Features

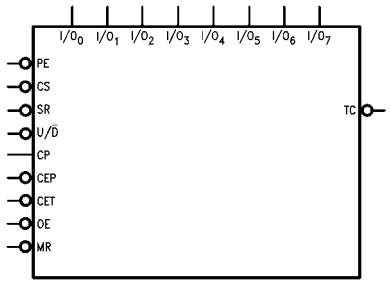
- Multiplexed 3-STATE I/O ports
- Built-in lookahead carry capability
- Count frequency 100 MHz typical
- Supply current 75 mA typical
- Guaranteed 4000V minimum ESD protection

Ordering Code:

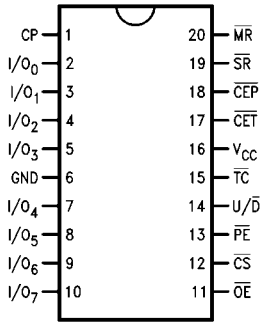
Order Number	Package Number	Package Description
74F579SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F579SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F579PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" tot he ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

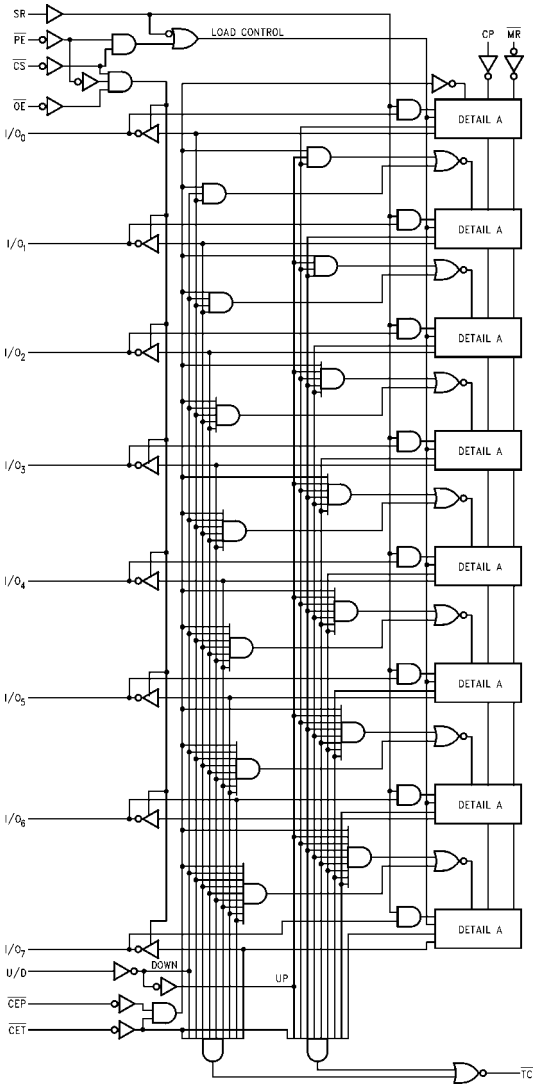
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I/O_0–I/O_7	Data Inputs or	3.5/0.333	70 µA/–0.2 mA
	3-STATE Outputs	75/15	–3 mA/24 mA
$\overline{PE}$	Parallel Enable Input (Active LOW)	0.25/0.333	5 µA/–0.2 mA
U/$\overline{D}$	Up-Down Count Control Input	0.25/0.333	5 µA/–0.2 mA
$\overline{MR}$	Master Reset Input (Active LOW)	0.25/0.333	5 µA/–0.2 mA
$\overline{SR}$	Synchronous Reset Input (Active LOW)	0.25/0.333	5 µA/–0.2 mA
$\overline{CEP}$	Count Enable Parallel Input (Active LOW)	0.25/0.333	5 µA/–0.2 mA
$\overline{CET}$	Count Enable Trickle Input (Active LOW)	0.25/0.333	5 µA/–0.2 mA
$\overline{CS}$	Chip Select Input Active (Active LOW)	0.25/0.333	5 µA/–0.2 mA
$\overline{OE}$	Output Enable Input (Active LOW)	0.25/0.333	5 µA/–0.2 mA
CP	Clock Pulse Input (Active Rising Edge)	0.25/0.333	5 µA/–0.2 mA
$\overline{TC}$	Terminal Count Output (Active LOW)	25/12.5	–1 mA/5 mA

Function Table

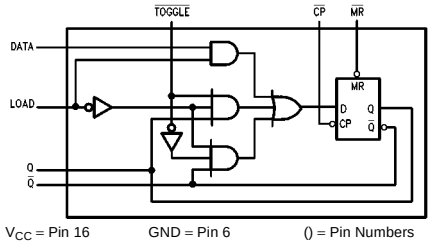
$\overline{MR}$	$\overline{SR}$	$\overline{CS}$	$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	U/$\overline{D}$	$\overline{OE}$	CP	Function
X	X	H	X	X	X	X	X	X	I/O_a to I/O_h in High Z ($\overline{PE}$ Disabled)
X	X	L	H	X	X	X	H	X	I/O_a to I/O_h in High Z
X	X	L	H	X	X	X	L	X	Flip-Flop Outputs Appear on I/O Lines
L	X	X	X	X	X	X	X	X	Asynchronous Reset for all Flip-Flops
H	L	X	X	X	X	X	X	⌐	Synchronous Reset for all Flip-Flops
H	H	L	L	X	X	X	X	⌐	Parallel Load all Flip-Flops
H	H	(Not LL)		H	X	X	X	⌐	Hold
H	H	(Not LL)		X	H	X	X	⌐	Hold ($\overline{TC}$ Held HIGH)
H	H	(Not LL)		L	L	H	X	⌐	Count Up
H	H	(Not LL)		L	L	L	X	⌐	Count Down

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW to HIGH Clock Transition
Not LL = $\overline{CS}$ and $\overline{PE}$ should never both be LOW voltage level at the same time.

Logic Diagrams



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.



V_{CC} = Pin 16 GND = Pin 6 () = Pin Numbers

Detail A

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		5% V_{CC}	2.7					
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA ($\overline{TC}$), I_{OL} = 24 mA (I/O_n)
		5% V_{CC}			0.5			I_{OL} = 20 mA ($\overline{TC}$), I_{OL} = 24 mA (I/O_n)
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (I/O_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Control				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{ZZ}	Bus Drainage Test				500	µA	0.0	V_{OUT} = 5.25V
I_{IL}	Input LOW Current				−0.2	mA	Max	V_{IN} = 0.5V (Non-I/O Pins)
I_{IH} & I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (I/O_n)
I_{IL} & I_{OZL}	Output Leakage Current				−200	µA	Max	V_{OUT} = 0.5V (I/O_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			70	110	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			85	120	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			85	125	mA	Max	V_O = HIGH Z

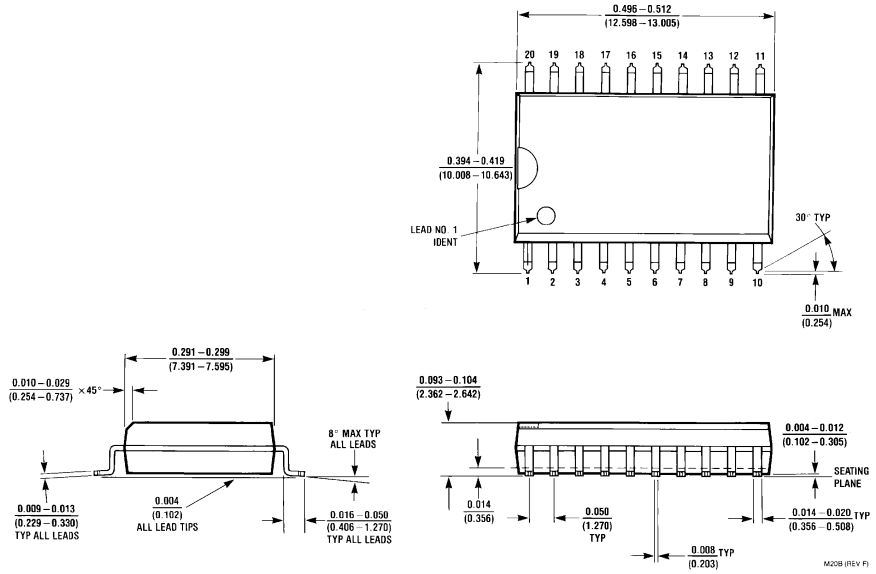
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	70	85		80		
t_{PLH}	Propagation Delay	3.0	5.0	7.5	3.0	8.0	ns
t_{PHL}	CP to I/O_n	5.0	8.0	11.5	5.0	11.5	
t_{PLH}	Propagation Delay	5.0	7.5	11.5	5.0	12.0	ns
t_{PHL}	CP to $\overline{TC}$	5.0	7.0	11.5	5.0	12.0	
t_{PLH}	Propagation Delay	4.5	7.0	9.0	4.5	10.0	ns
t_{PHL}	$U/\overline{D}$ to $\overline{TC}$	4.5	8.0	9.5	4.5	10.0	
t_{PLH}	Propagation Delay	2.5	3.8	6.0	2.5	6.5	ns
t_{PHL}	$\overline{CEP}$ or $\overline{CET}$ to $\overline{TC}$	3.5	6.0	8.0	3.5	8.5	
t_{PHL}	Propagation Delay $\overline{MR}$ to I/O_n	5.0	7.5	10.0	5.0	10.0	ns
t_{PHL}	Propagation Delay $\overline{MR}$ to TC	6.5	10.0	13.0	6.5	13.5	ns
t_{PZH}	Output Enable Time	3.0	5.0	8.5	3.0	9.0	ns
t_{PZL}	$\overline{CS}$ or $\overline{PE}$ to I/O	5.5	8.0	10.5	5.5	11.5	
t_{PHZ}	Output Disable Time	2.0	5.0	8.5	2.0	9.0	ns
t_{PLZ}	$\overline{CS}$ or $\overline{PE}$ to I/O	2.0	4.5	8.0	2.0	8.5	
t_{PZH}	Output Enable Time	3.0	5.0	8.0	3.0	8.5	ns
t_{PZL}	$\overline{OE}$ to I/O_n	5.0	8.0	11.0	5.0	12.0	
t_{PHZ}	Output Disable Time	2.0	4.0	6.5	2.0	6.5	ns
t_{PLZ}	$\overline{OE}$ to I/O_n	2.0	4.0	6.0	2.0	6.5	

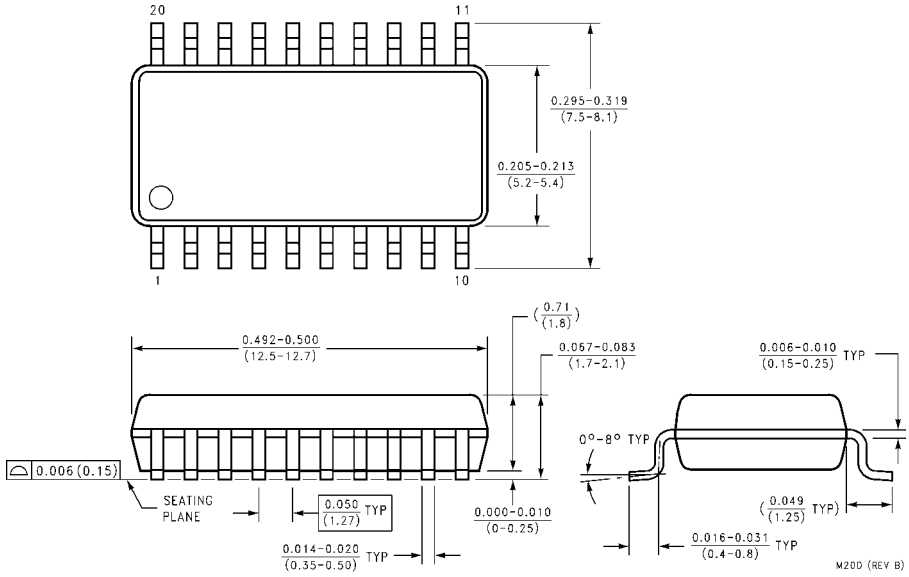
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Typ	Max	Min	Max	
$t_S(H)$	Setup Time	4.0			4.0		ns
$t_S(L)$	I/O_n to CP	4.0			4.0		
$t_H(H)$	Hold Time	0.0			0.0		ns
$t_H(L)$	I/O_n to CP	0.0			0.0		
$t_S(H)$	Setup Time	9.5			9.5		ns
$t_S(L)$	$\overline{PE}$, $\overline{CS}$ or $\overline{SR}$ to CP	9.5			9.5		
$t_H(H)$	Hold Time	0.0			0.0		ns
$t_H(L)$	$\overline{PE}$, $\overline{CS}$ or $\overline{SR}$ to CP	0.0			0.0		
$t_S(H)$	Setup Time	6.5			6.5		ns
$t_S(L)$	$\overline{CET}$ or $\overline{CEP}$ to CP	9.5			9.5		
$t_H(H)$	Hold Time	0.0			0.0		ns
$t_H(L)$	$\overline{CET}$ or $\overline{CEP}$ to CP	0.0			0.0		
$t_S(H)$	Setup Time	9.0			9.5		ns
$t_S(L)$	$U/\overline{D}$ to CP	9.0			9.5		
$t_H(H)$	Hold Time	0.0			0.0		ns
$t_H(L)$	$U/\overline{D}$ to CP	0.0			0.0		
$t_W(H)$	Clock Pulse Width	4.5			4.5		ns
$t_W(L)$	HIGH or LOW	4.5			4.5		
$t_W(L)$	$\overline{MR}$ Pulse Width	3.0			3.0		ns
t_{REC}	Recovery Time $\overline{MR}$ to CP	4.0			4.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

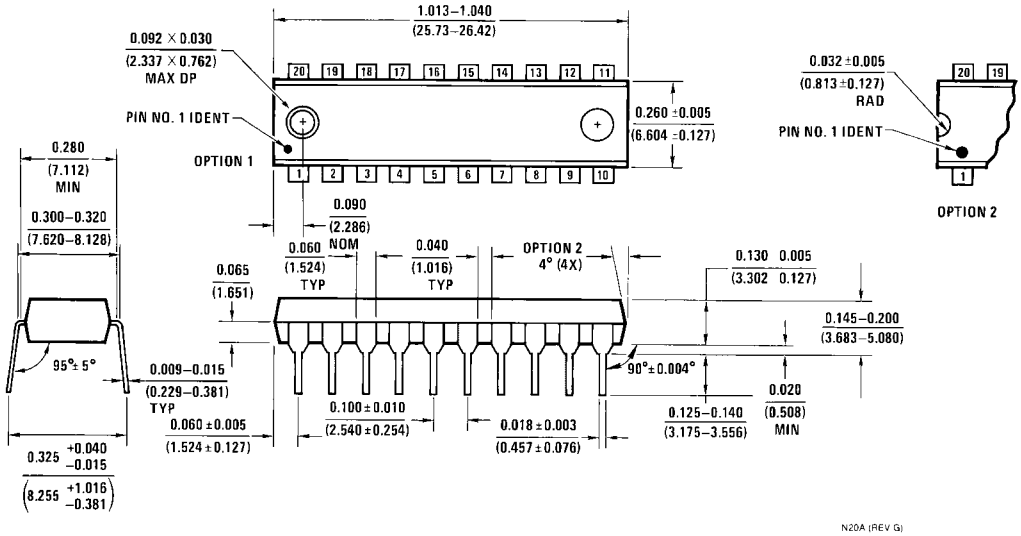


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised March 1999

74F583
4-Bit BCD Adder

General Description

The 'F583 high-speed 4-bit, BCD full adder with internal carry lookahead accepts two 4-bit decimal numbers (A_0–A_3, B_0–B_3) and a Carry Input (C_n). It generates the decimal sum outputs (S_0–S_3), and a Carry Output (C_{n+4}) if the sum is greater than 9. The 'F583 is the functional equivalent of the 82S83.

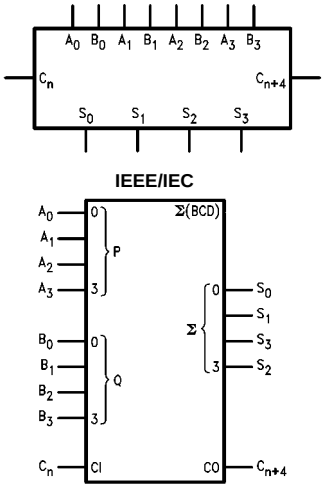
Features

- Adds two decimal numbers
- Full internal lookahead
- Fast ripple carry for economical expansion
- Sum output delay time 16.5 ns max
- Ripple carry delay time 8.5 ns max
- Input to ripple delay time 14.0 ns max
- Supply current 60 mA max

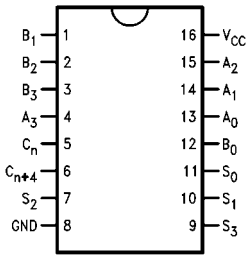
Ordering Code:

Order Number	Package Number	Package Description
74F583SC	M16B	16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F583PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

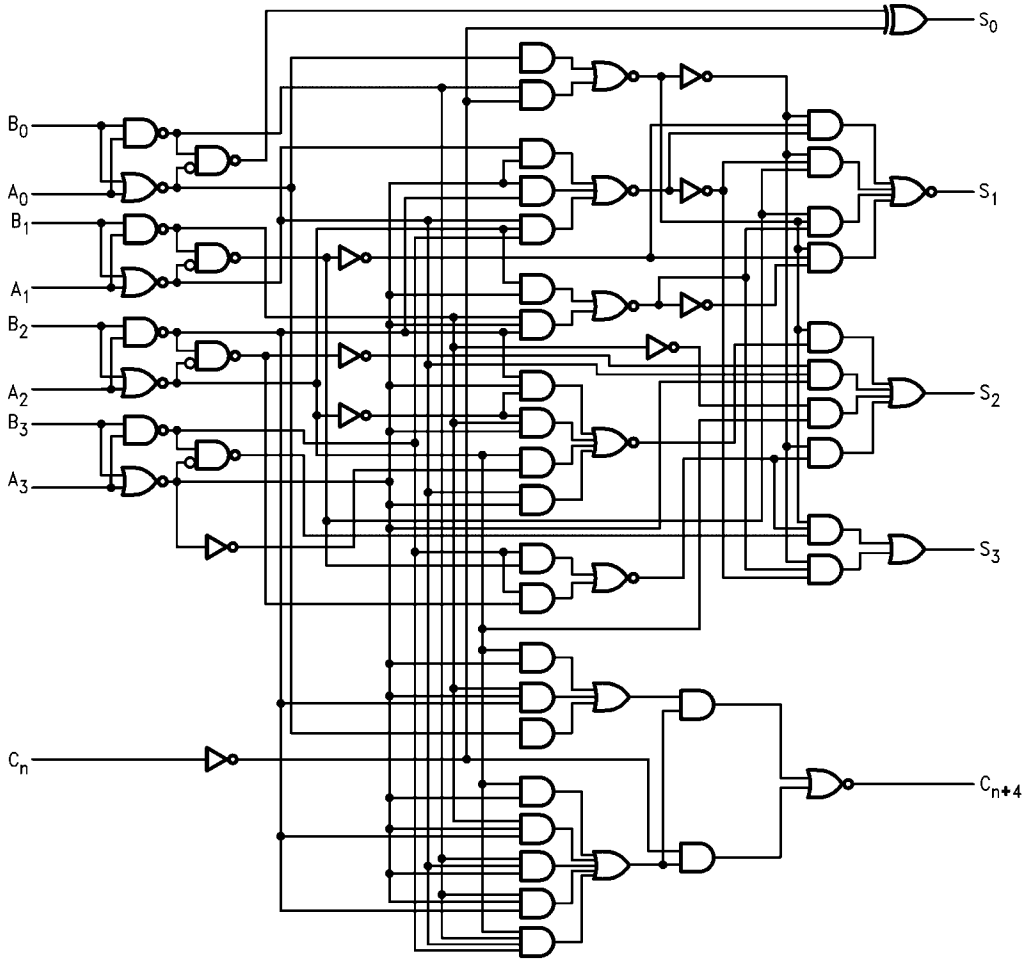
Pin Names	Description	74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_3	A Operand Inputs	1.0/2.0	20 µA/–1.2 mA
B_0–B_3	B Operand Inputs	1.0/2.0	20 µA/–1.2 mA
C_n	Carry Input	1.0/1.0	20 µA/–0.6 mA
S_0–S_3	Sum Outputs	50/33.3	–1 mA/20 mA
C_{n+4}	Carry Output	50/33.3	–1 mA/20 mA

Functional Description

The 'F583 4-bit binary coded (BCD) full adder performs the addition of two decimal numbers (A_0–A_3, B_0–B_3). The lookahead generates the BCD carry terms internally, allowing the 'F583 to then do BCD addition correctly. For BCD numbers 0 through 9 at A and B inputs, the BCD sum forms at the output. In the addition of two BCD numbers totalling a number greater than 9, a valid BCD number and a carry will result.

For input values larger than 9, the number is converted from binary to BCD. Binary to BCD conversion occurs by grounding one set of inputs, A_n or B_n, and applying any 4-bit binary number to the other set of inputs. If the input is between 0 and 9, a BCD number occurs at the output. If the binary input falls between 10 and 15, a carry term is generated. Both the carry term and the sum are the BCD equivalent of the binary input. Converting binary numbers greater than 16 may be achieved through cascading 'F583s.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC}Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	0°C to +70°C
Supply Voltage	
Commercial	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

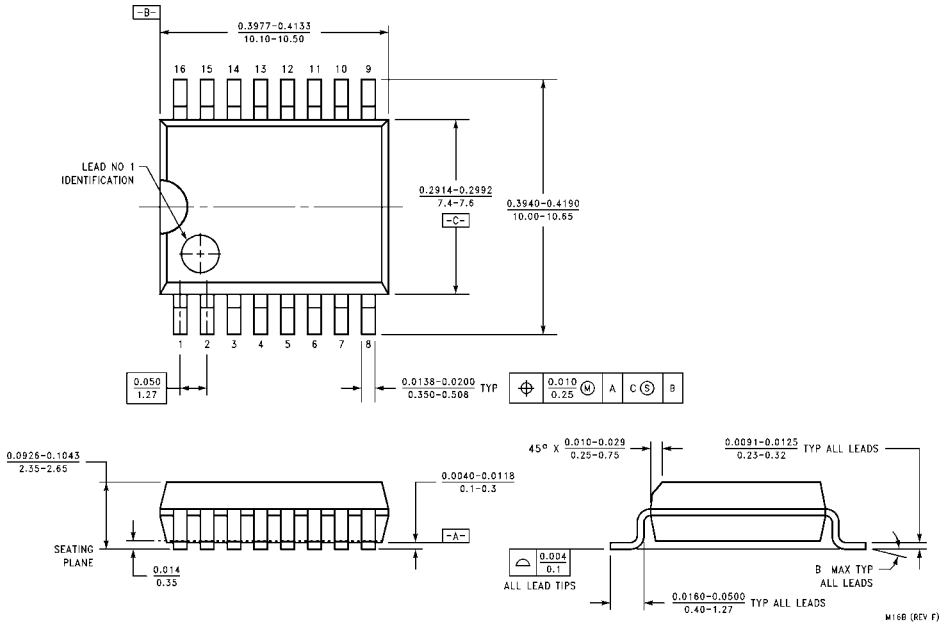
DC Electrical Characteristics

Symbol	Parameter		74F			Units	V_{CC}	Conditions
			Min	Typ	Max			
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	74F 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		74F 5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	74F 10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				20	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (C_n)
					−1.2			V_{IN} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC}
I_{CCL}	Power Supply Current			40	60	mA	Max	V_O = LOW

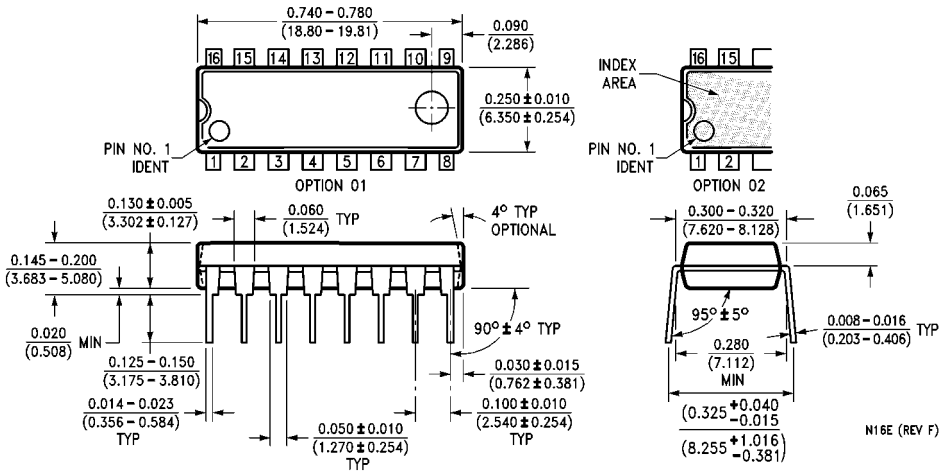
AC Electrical Characteristics

Symbol	Parameter	74F T_A = +25°C V_{CC} = +5.0V C_L = 50 pF			74F T_A, V_{CC} = Com C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	13.0	16.5	2.5	17.5	ns
t_{PHL}	A_n or B_n to S_n	2.5	11.0	14.0	2.5	15.0	
t_{PLH}	Propagation Delay	2.5	6.5	8.5	2.5	9.5	ns
t_{PHL}	C_n to C_{n+4}	2.5	5.0	6.5	2.5	7.5	
t_{PLH}	Propagation Delay	4.0	11.0	14.0	4.0	15.0	ns
t_{PHL}	A_n or B_n to C_{n+4}	4.0	8.0	10.5	4.0	11.5	

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M16B



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F620 • 74F623
Inverting Octal Bus Transceiver with 3-STATE Outputs

General Description

These devices are octal bus transceivers designed for asynchronous two-way data flow between the A and B busses. Both busses are capable of sinking 64 mA and have 3-STATE outputs. Dual enable pins (GAB, $\overline{G}$BA) allow data transmission from the A bus to the B bus or from the B bus to the A bus. The 74F620 is an inverting option of the 74F623.

Features

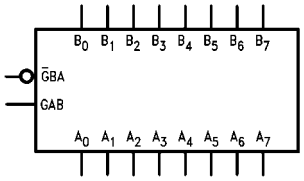
- Designed for asynchronous two-way data flow between busses
- Outputs sink 64 mA
- Dual enable inputs control direction of data flow
- Guaranteed 4000V minimum ESD protection
- 74F620 is an inverting option of the 74F623

Ordering Code:

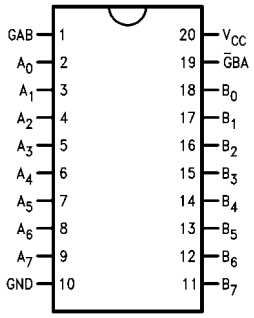
Order Number	Package Number	Package Description
74F620PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F623SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F623PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



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Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{G}$BA, GAB	Enable Inputs	1.0/1.0	20 µA/–0.6 mA
A_0–A_7	A Inputs or	3.5/1.083	70 µA/–0.4 mA
	3-STATE Outputs	150/40	–3 mA/64 mA
B_0–B_7	B Inputs or	3.5/1.083	70 µA/–0.4 mA
	3-STATE Outputs	150/40	–3 mA/64 mA

Functional Description

The enable inputs GAB and $\overline{G}$BA control whether data is transmitted from the A bus to the B bus or from the B bus to the A bus. If both $\overline{G}$BA and GAB are disabled ($\overline{G}$BA HIGH and GAB LOW), the outputs are in the high impedance state and data is stored at the A and B busses. When $\overline{G}$BA is active LOW, B data is sent to the A bus. When GAB is active HIGH, data from the A bus is sent to the B bus. If both enable inputs are active ($\overline{G}$BA LOW and GAB HIGH) B data is sent to the A bus while A data is sent to the B bus.

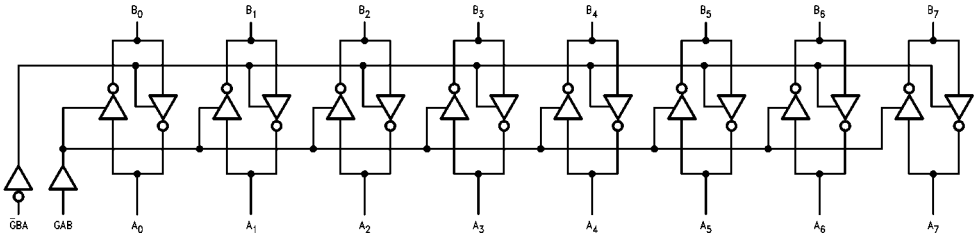
Function Table

Enable Inputs		Operation	
$\overline{G}$BA	GAB	74F620	74F623
L	L	$\overline{B}$ Data to A Bus	B Data to A Bus
H	H	$\overline{A}$ Data to B Bus	A Data to B Bus
H	L	Z	Z
L	H	$\overline{B}$ Data to A Bus, $\overline{A}$ Data to B Bus	B Data to A Bus, A Data to B Bus

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance

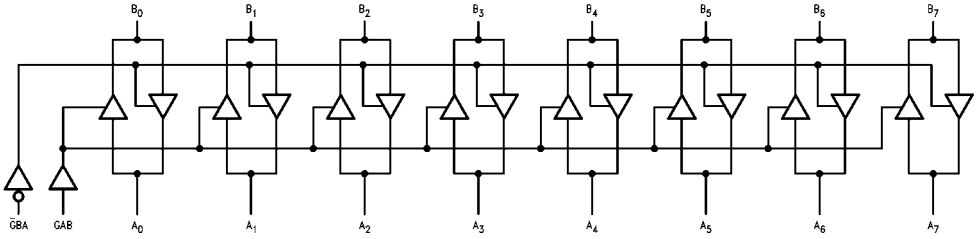
Logic Diagrams

74F620



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

74F623



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

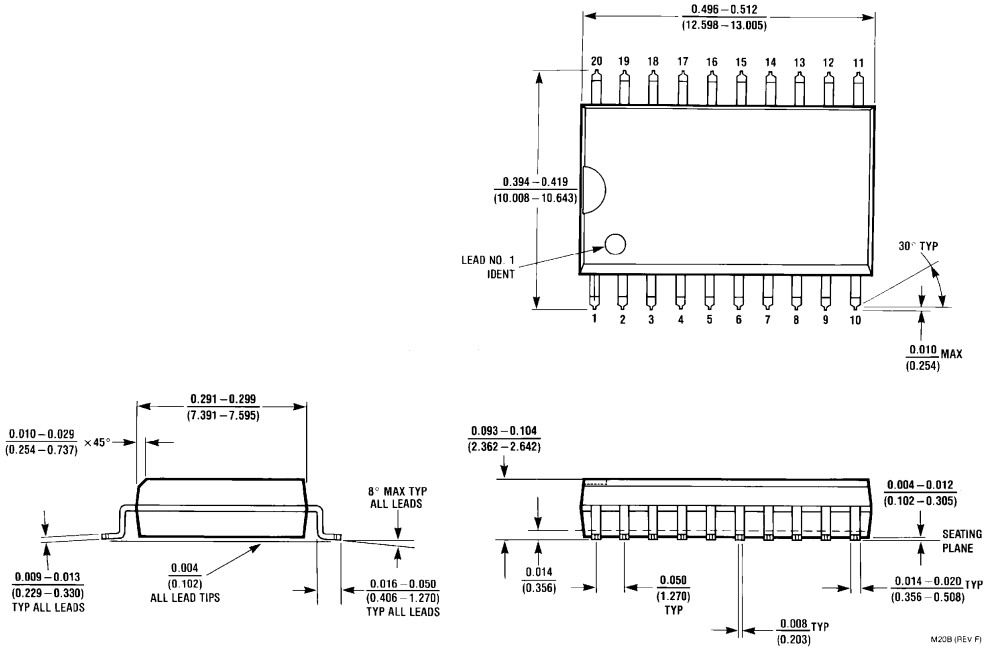
DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage 10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage 10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V (GBA, GAB)
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current (74F620)			82	mA	Max	V_O = HIGH, V_{IN} = 0.2V
I_{CCL}	Power Supply Current (74F620)			82	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F620)			95	mA	Max	V_O = HIGH Z
I_{CCH}	Power Supply Current (74F623)			65	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F623)			82	mA	Max	V_O = LOW, V_{IN} = 0.2V
I_{CCZ}	Power Supply Current (74F623)			85	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

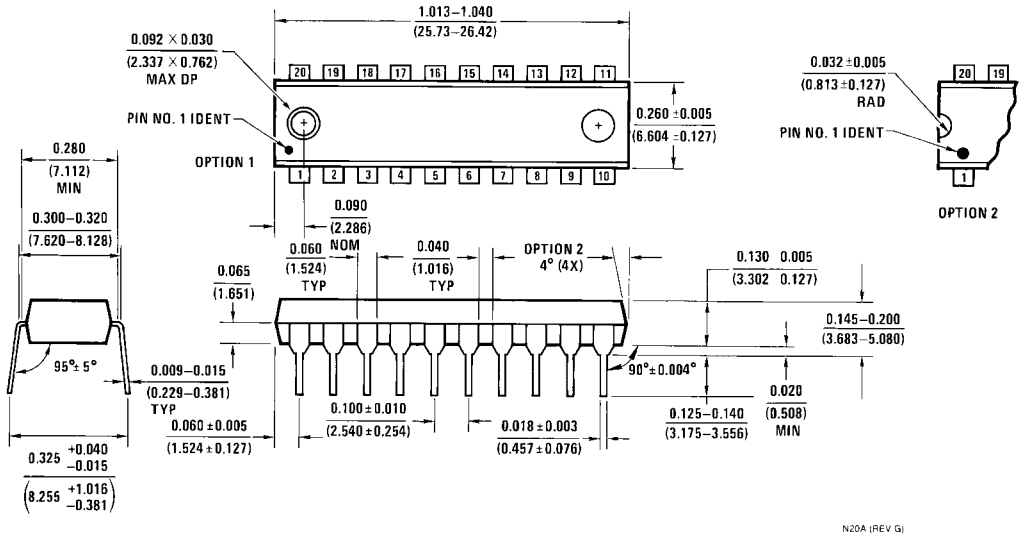
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5		7.5	2.0	8.0	ns
t_{PHL}	A Input to B Output (74F620)	2.0		7.0	2.0	7.0	
t_{PLH}	Propagation Delay	2.5		7.5	2.0	8.0	ns
t_{PHL}	B Input to A Output (74F620)	2.0		7.0	2.0	7.0	
t_{PLH}	Propagation Delay	1.5		6.5	1.5	7.5	ns
t_{PHL}	A Input to B Output (74F623)	2.0		7.0	2.0	7.5	
t_{PLH}	Propagation Delay	1.5		6.5	1.5	7.5	ns
t_{PHL}	B Input to A Output (74F623)	2.0		7.0	2.0	7.5	
t_{PZH}	Enable Time	2.0		7.0	2.0	8.0	ns
t_{PZL}	$\overline{G}$BA Input to A Output	2.5		8.0	2.0	8.5	
t_{PHZ}	Disable Time	1.5		6.5	1.5	7.5	
t_{PLZ}	$\overline{G}$BA Input to A Output	1.0		5.5	1.0	5.5	
t_{PZH}	Enable Time	2.0		7.5	2.0	8.5	ns
t_{PZL}	GAB Input to B Output (74F620)	3.0		8.0	2.0	8.5	
t_{PHZ}	Disable Time	2.5		8.0	2.0	9.0	
t_{PLZ}	GAB Input to B Output (74F620)	2.0		7.5	2.0	8.0	
t_{PZH}	Enable Time	2.0		7.5	2.0	8.5	ns
t_{PZL}	GAB Input to B Output (74F623)	2.5		8.0	2.0	8.5	
t_{PHZ}	Disable Time	2.0		8.0	2.0	9.0	
t_{PLZ}	GAB Input to B Output (74F623)	2.0		8.0	2.0	8.0	

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised March 1999

74F64
4-2-3-2-Input AND-OR-Invert Gate

General Description

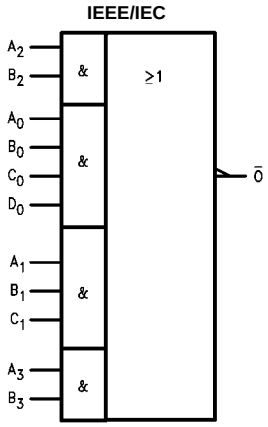
This device contains gates configured to perform a 4-2-3-2 input AND-OR-INVERT function.

Ordering Code:

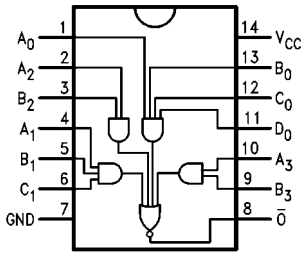
Order Number	Package Number	Package Description
74F64SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F64SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F64PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n, C_n, D_n	Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{O}$	Output	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

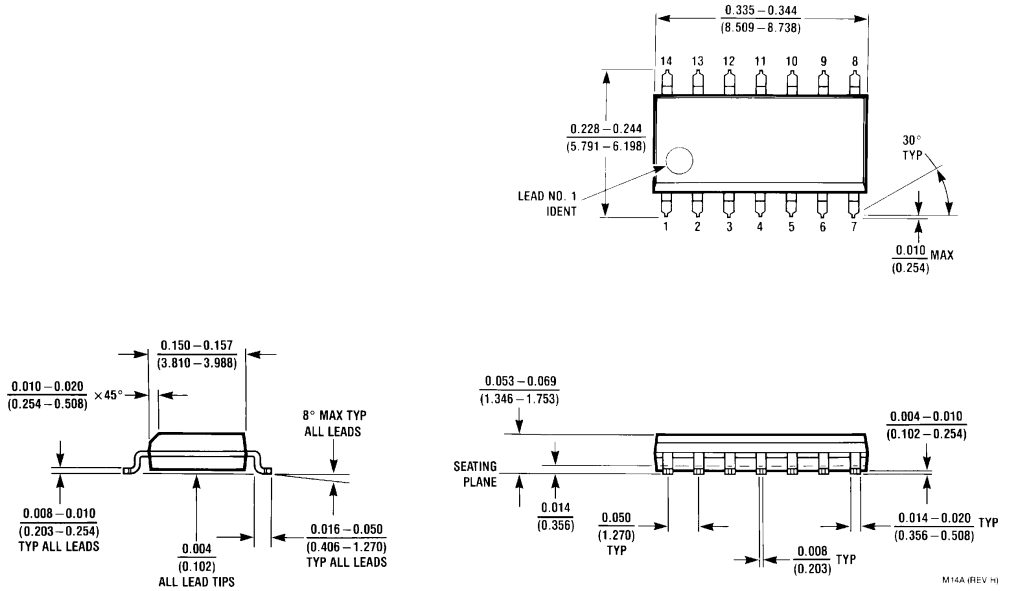
DC Electrical Characteristics

Symbol	Parameter		Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage		V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage		V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	V	Min	I_{OH} = −1 mA
	Voltage	5% V_{CC}			I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current		µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test		µA	Max	V_{IN} = 7.0V
I_{CEX}	Output High Leakage Current		µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current		µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current		mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current		mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		mA	Max	V_O = LOW

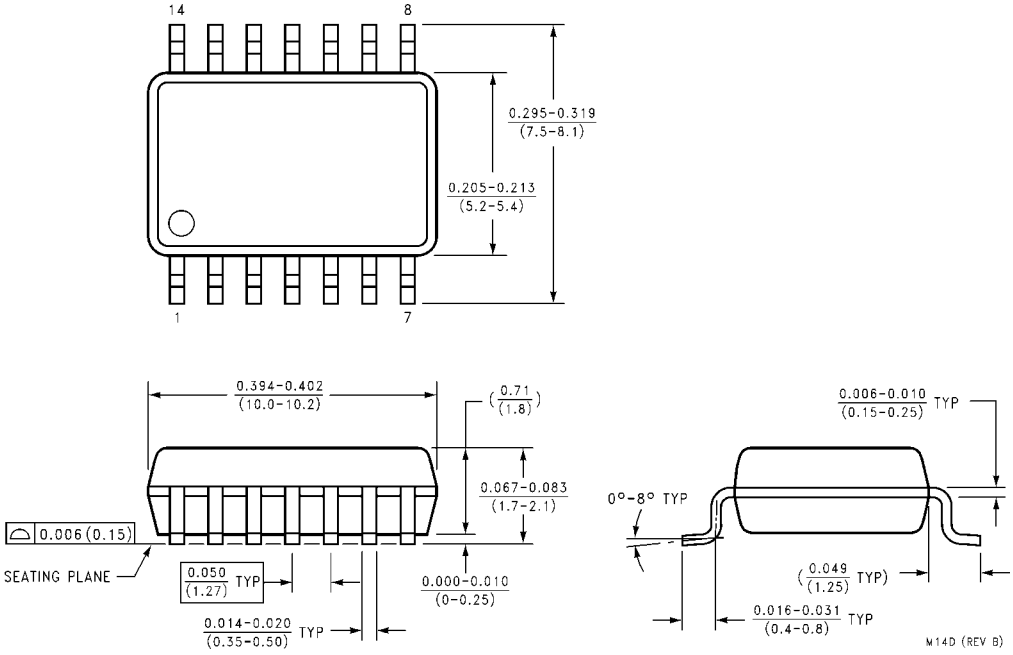
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0° to +70°C, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.6	6.5	2.5	7.5	ns
t_{PHL}	A_n, B_n, C_n, D_n to $\overline{O}$	1.5	3.2	4.5	1.5	5.5	

Physical Dimensions inches (millimeters) unless otherwise noted

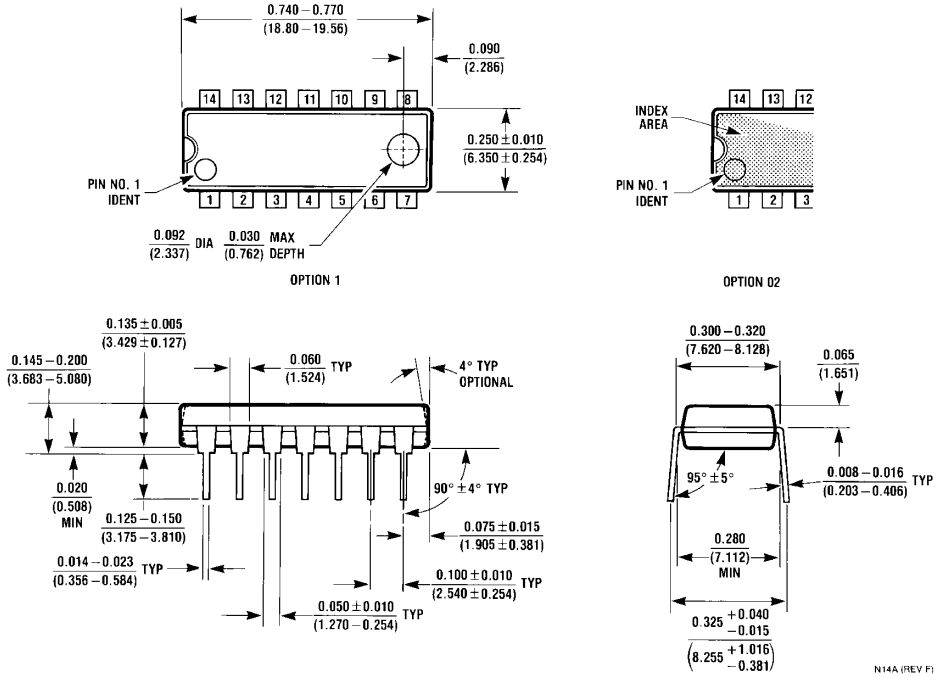


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1989
Revised August 1999

74F640 • 74F645
Octal Bus Transceiver with 3-STATE Outputs

General Description

These devices are octal bus transceivers designed for asynchronous two-way data flow between the A and B busses. Both busses are capable of sinking 64 mA, have 3-STATE outputs, and a common output enable pin. The direction of data flow is determined by the transmit/receive ($T/\overline{R}$) input. The 74F645 is a high speed/low power version of the 74F245. The 74F640 is an inverting option of the 74F645.

Features

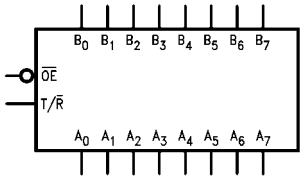
- Designed for asynchronous two-way data flow between busses
- Outputs sink 64 mA
- Transmit/receive ($T/\overline{R}$) input controls the direction of data flow
- 74F645 is a lower power, faster version of the 74F245
- 74F640 is an inverting option of the 74F645

Ordering Code:

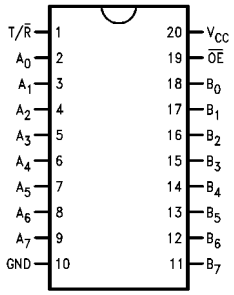
Order Number	Package Number	Package Description
74F640SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F640PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74F645PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$T/\overline{R}$	Transmit/Receive Input	1.0/1.0	20 μA/–0.6 mA
A_0–A_7	Side A Inputs or	3.5/0.667	70 μA/–0.4 mA
	3-STATE Outputs	600/106.6	–12 mA/64 mA
B_0–B_7	Side B Inputs or	3.5/0.667	70 μA/–0.4 mA
	3-STATE Outputs	600/106.6	–12 mA/64 mA

Functional Description

The output enable ($\overline{OE}$) is active LOW. If the device is disabled ($\overline{OE}$ HIGH), the outputs are in the high impedance state. The transmit/receive input ($T/\overline{R}$) controls whether data is transmitted from the A bus to the B bus or from the B bus to the A bus. When $T/\overline{R}$ is LOW, B data is sent to the A bus. If $T/\overline{R}$ is HIGH, A data is sent to the B bus.

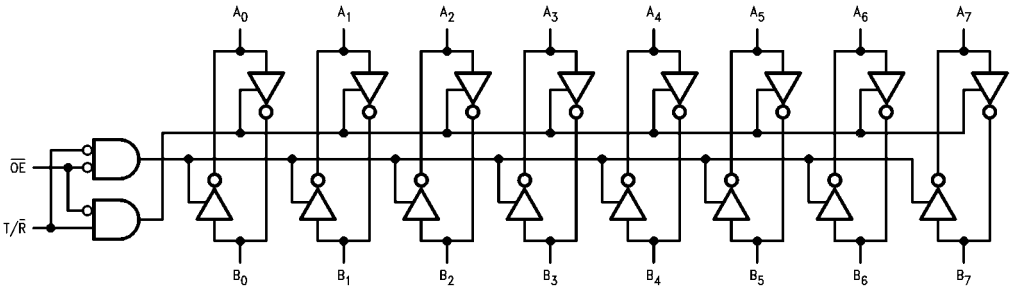
Function Table

Inputs		Outputs	
$\overline{OE}$	$T/\overline{R}$	74F640	74F645
L	L	Bus $\overline{B}$ data to Bus A	Bus B data to Bus A
L	H	Bus $\overline{A}$ data to Bus B	Bus A data to Bus B
H	X	Z	Z

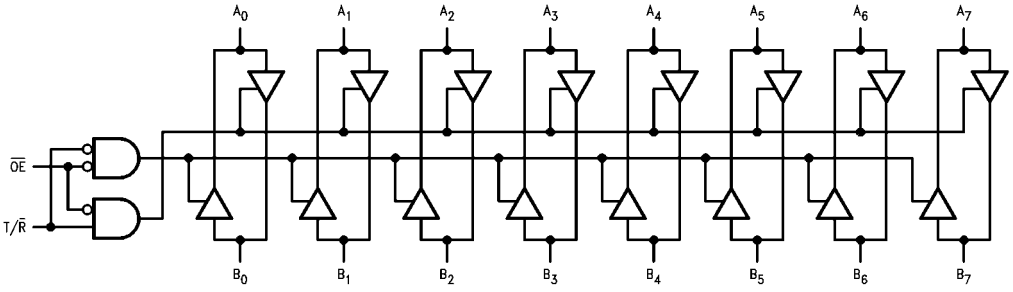
H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High Impedance State

Logic Diagram

74F640



74F645



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage 10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage 10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V (Non I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V (Non I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25
I_{CCH}	Power Supply Current (74F640)			80	mA	Max	V_O = HIGH, V_{IN} = 0.2V
I_{CCL}	Power Supply Current (74F640)			80	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F640)			96	mA	Max	V_O = HIGH Z
I_{CCH}	Power Supply Current (74F645)			65	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F645)			80	mA	Max	V_O = LOW, V_{IN} = 0.2V
I_{CCZ}	Power Supply Current (74F645)			90	mA	Max	V_O = HIGH Z

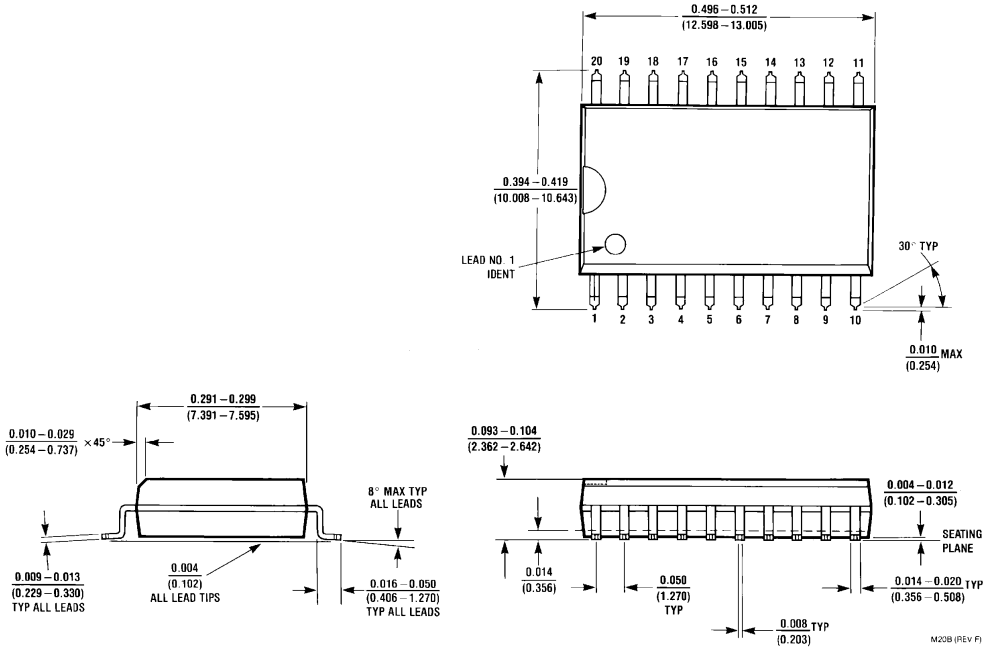
AC Electrical Characteristics 74F640

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5		7.5	2.0	8.0	ns
t_{PHL}	A Input to B Output	2.0		7.0	2.0	7.0	
t_{PLH}	Propagation Delay	2.5		7.5	2.0	8.0	ns
t_{PHL}	B Input to A Output	2.0		7.0	2.0	7.0	
t_{PZH}	Enable Time	2.5		7.5	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ Input to A Output	2.5		8.0	2.0	8.5	
t_{PHZ}	Disable Time	1.5		7.0	1.0	7.5	
t_{PLZ}	$\overline{OE}$ Input to A Output	1.5		6.0	1.5	6.0	
t_{PZH}	Enable Time	2.5		7.5	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ Input to B Output	2.5		8.0	2.0	8.5	
t_{PHZ}	Disable Time	1.5		7.0	1.0	7.5	
t_{PLZ}	$\overline{OE}$ Input to B Output	1.5		6.0	1.5	6.0	

AC Electrical Characteristics 74F645

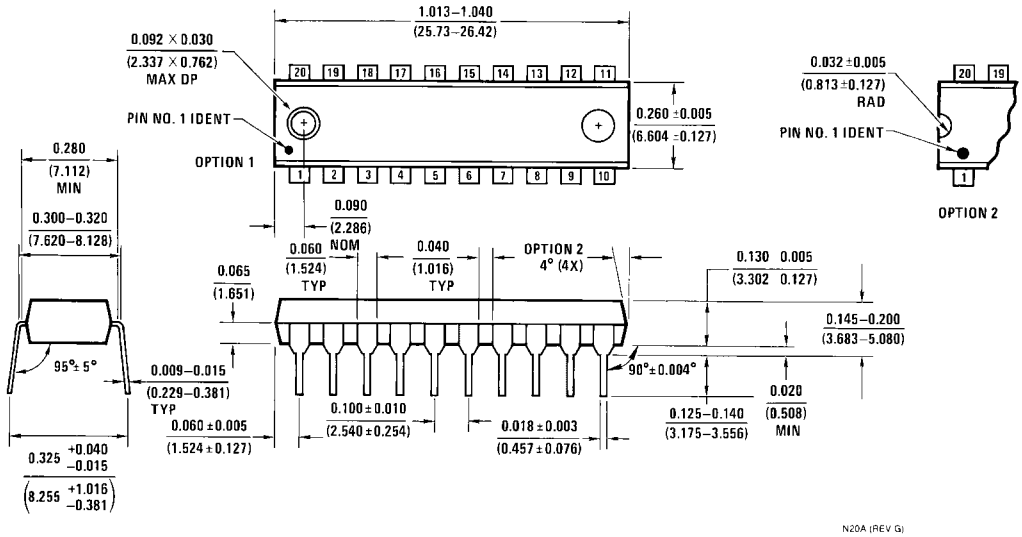
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5		6.0	1.5	7.0	ns
t_{PHL}	A Input to B Output	2.0		7.0	2.0	7.5	
t_{PLH}	Propagation Delay	1.5		6.0	1.5	7.0	ns
t_{PHL}	B Input to A Output	2.0		7.0	2.0	7.5	
t_{PZH}	Enable Time	2.5		8.0	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ Input to A Output	2.5		8.5	2.0	8.5	
t_{PHZ}	Disable Time	1.5		7.0	1.0	8.0	
t_{PLZ}	$\overline{OE}$ Input to A Output	1.0		5.5	1.0	5.5	
t_{PZH}	Enable Time	2.5		7.5	2.0	9.5	ns
t_{PZL}	$\overline{OE}$ Input to B Output	2.5		8.5	2.5	9.0	
t_{PHZ}	Disable Time	1.5		6.5	1.0	7.5	
t_{PLZ}	$\overline{OE}$ Input to B Output	1.0		5.5	1.0	5.5	

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1988
Revised August 1999

74F646 • 74F646B • 74F648
Octal Transceiver/Register with 3-STATE Outputs

General Description

These devices consist of bus transceiver circuits with 3-STATE, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a high logic level. Control $\overline{G}$ and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control $\overline{G}$ is Active LOW. In the isolation mode (control $\overline{G}$ HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

Features

- Independent registers for A and B buses
- Multiplexed real-time and stored data
- 74F648 has inverting data paths
- 74F646/74F646B have non-inverting data paths
- 74F646B is a faster version of the 74F646
- 3-STATE outputs
- 300 mil slim DIP

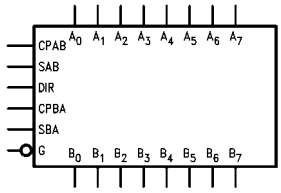
Ordering Code:

Order Number	Package Number	Package Description
74F646SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F646MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74F646SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
74F646BSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F646BSPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
74F648SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F648SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

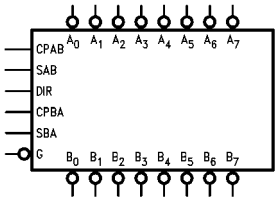
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols

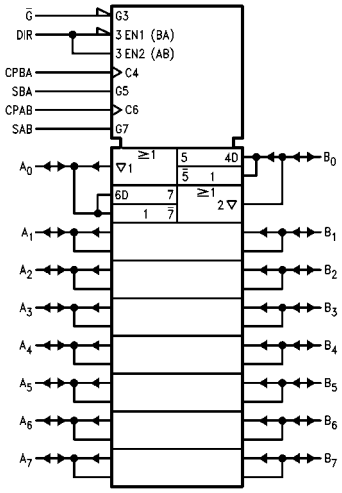
74F646/74F646B



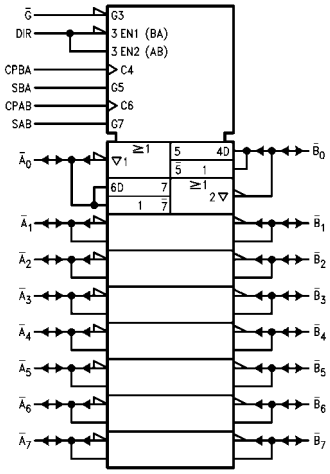
74F648



IEEE/IEC
74F646/74F646B

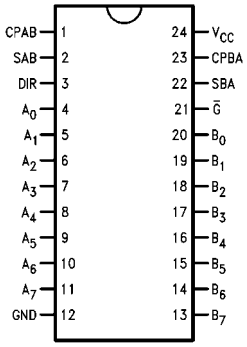


IEEE/IEC
74F648



Connection Diagrams

74F646/74F646B



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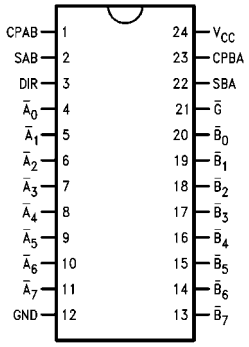


Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Data Register A Inputs/	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
B_0–B_7	Data Register B Inputs/	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
CPAB, CPBA	Clock Pulse Inputs	1.0/1.0	20 µA/–0.6 mA
SAB, SBA	Select Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{G}$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
DIR	Direction Control Input	1.0/1.0	20 µA/–0.6 mA

Function Table

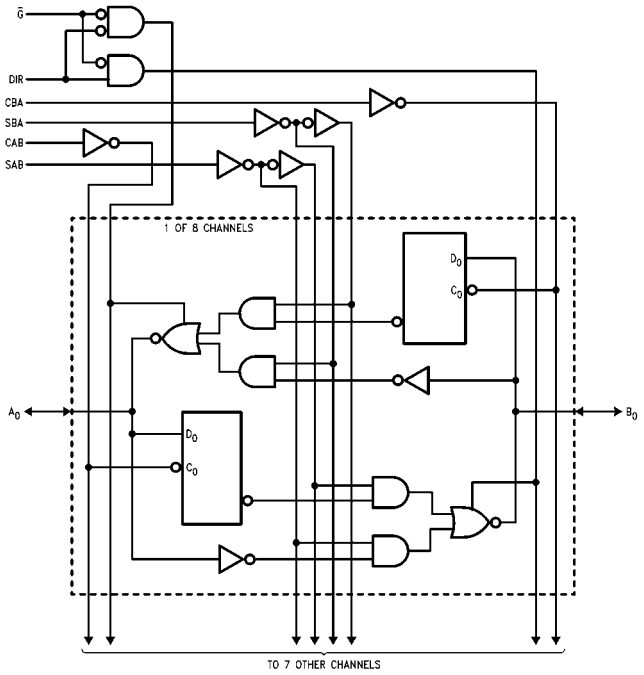
Inputs						Data I/O (Note 1)		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Irrelevant
↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR Inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the clock inputs.

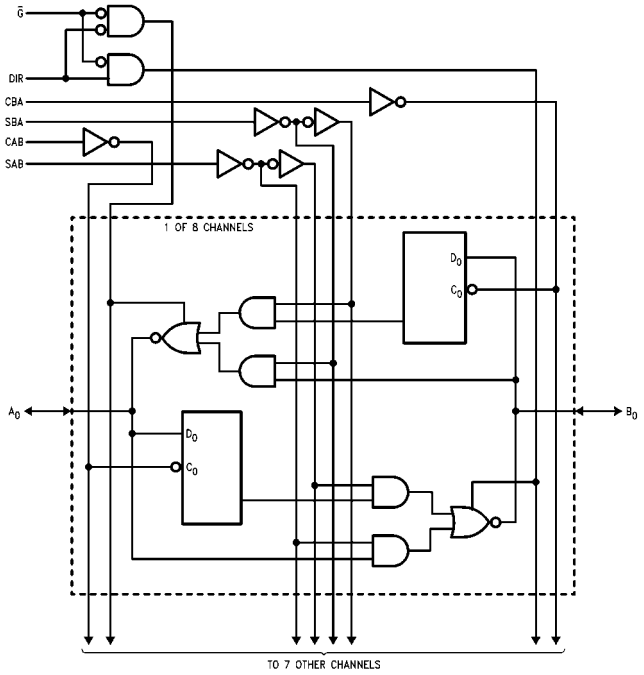
Logic Diagrams

74F646/74F646B



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

74F648



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage 10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage 10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V (Non I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V (Non I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			135	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			150	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			150	mA	Max	V_O = HIGH Z

AC Electrical Characteristics 74F646/74F648

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	90		75		90		MHz
t_{PLH}	Propagation Delay	2.0	7.0	2.0	8.5	2.0	8.0	ns
t_{PHL}	Clock to Bus	2.0	8.0	2.0	9.5	2.0	9.0	
t_{PLH}	Propagation Delay	1.0	7.0	1.0	8.0	1.0	7.5	ns
t_{PHL}	Bus to Bus (74F646)	1.0	6.5	1.0	8.0	1.0	7.0	
t_{PLH}	Propagation Delay	2.0	8.5	1.0	10.0	2.0	9.0	ns
t_{PHL}	Bus to Bus (74F648)	1.0	7.5	1.0	9.0	1.0	8.0	
t_{PLH}	Propagation Delay	2.0	8.5	2.0	11.0	2.0	9.5	ns
t_{PHL}	SBA or SAB to A or B	2.0	8.0	2.0	10.0	2.0	9.0	
t_{PZH}	Enable Time	2.0	8.5	2.0	10.0	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ to A or B	2.0	12.0	2.0	13.5	2.0	12.5	
t_{PHZ}	Disable Time	1.0	7.5	1.0	9.0	1.0	8.5	ns
t_{PLZ}	$\overline{OE}$ to A or B	2.0	9.0	2.0	11.0	2.0	9.5	
t_{PZH}	Enable Time	2.0	14.0	2.0	16.0	2.0	15.0	ns
t_{PZL}	DIR to A or B	2.0	13.0	2.0	15.0	2.0	14.0	
t_{PHZ}	Disable Time	1.0	9.0	1.0	10.0	1.0	9.5	ns
t_{PLZ}	DIR to A or B	2.0	11.0	2.0	12.0	2.0	11.5	

AC Operating Requirements 74F646/74F648

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	5.0		5.0		5.0		ns
$t_S(L)$	Bus to Clock	5.0		5.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.5		2.0		ns
$t_H(L)$	Bus to Clock	2.0		2.5		2.0		
$t_W(H)$	Clock Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		

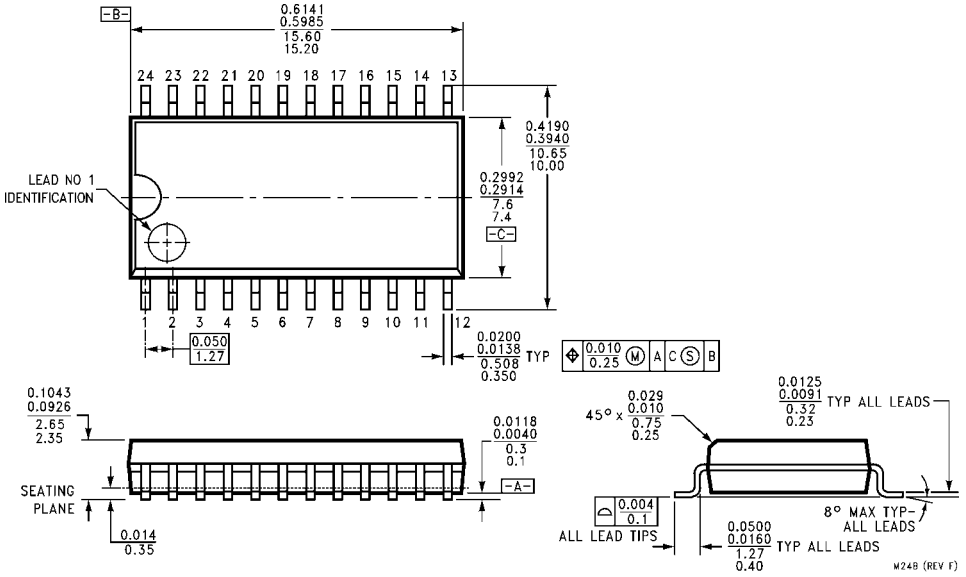
AC Electrical Characteristics 74F646B

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	165				150		MHz
t_{PLH}	Propagation Delay	2.5	7.0			2.5	8.0	ns
t_{PHL}	Clock to Bus	3.0	7.5			3.0	8.0	
t_{PLH}	Propagation Delay	2.0	6.0			2.0	7.0	ns
t_{PHL}	Bus to Bus	2.0	6.0			2.0	7.0	
t_{PLH}	Propagation Delay	2.5	7.5			2.5	8.5	ns
t_{PHL}	SBA or SAB to A or B	2.5	7.5			2.5	8.5	
t_{PZH}	Enable Time	2.5	6.5			2.5	8.0	ns
t_{PZL}	$\overline{OE}$ to A or B	2.5	9.0			2.5	10.0	
t_{PHZ}	Disable Time	1.5	6.5			1.5	7.5	ns
t_{PLZ}	$\overline{OE}$ to A or B	2.0	7.0			2.0	8.5	
t_{PZH}	Enable Time	2.0	7.0			2.0	8.5	ns
t_{PZL}	DIR to A or B	3.0	9.5			3.0	10.0	
t_{PHZ}	Disable Time	1.5	7.5			1.5	8.5	ns
t_{PLZ}	DIR to A or B	2.5	8.5			2.5	9.5	

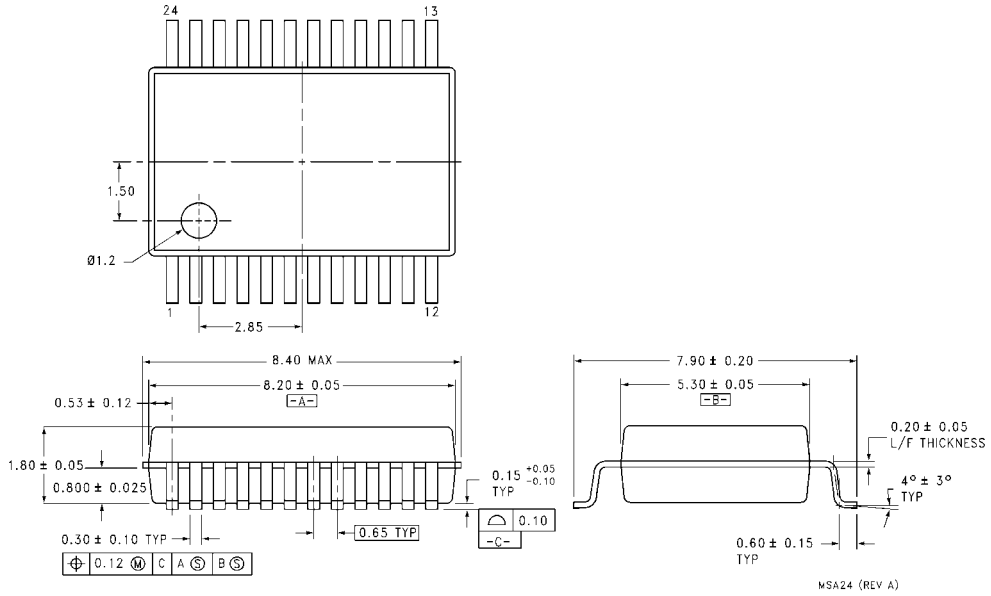
AC Operating Requirements 74F646B

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	5.0				4.0		ns
$t_S(L)$	Bus to Clock	5.0				4.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.5				1.5		ns
$t_H(L)$	Bus to Clock	1.5				1.5		
$t_W(H)$	Clock Pulse Width	5.0				5.0		ns
$t_W(L)$	HIGH or LOW	5.0				5.0		

Physical Dimensions inches (millimeters) unless otherwise noted

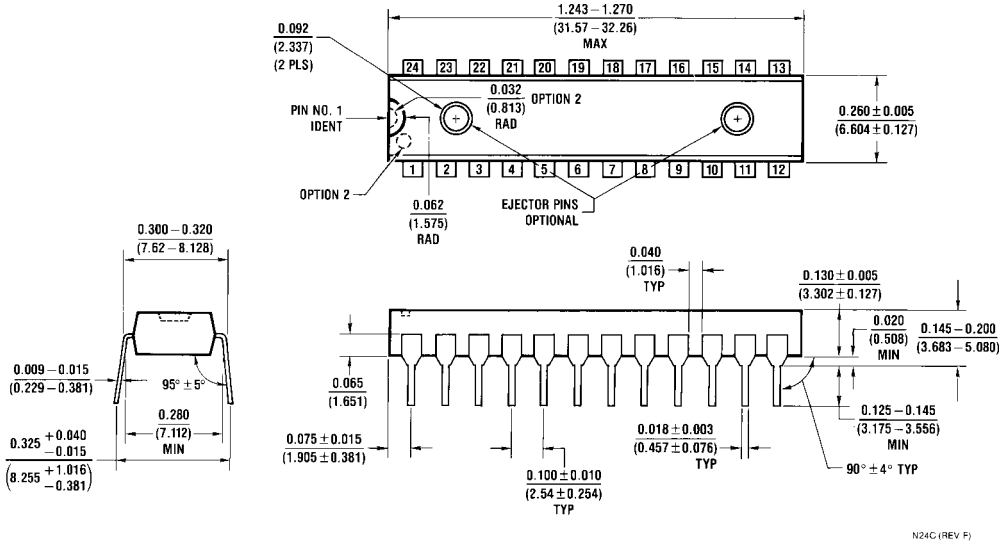


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

March 1988
Revised August 1999

74F651 • 74F652
Transceivers/Registers

General Description

These devices consist of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function.

Features

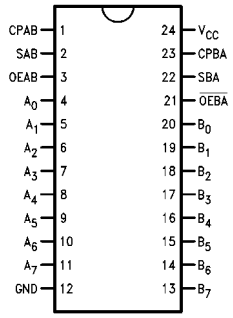
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- Choice of non-inverting and inverting data paths
  - 74F651 inverting
  - 74F652 non-inverting

Ordering Code:

Order Number	Package Number	Package Description
74F651SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F651SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
74F652SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F652SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbols

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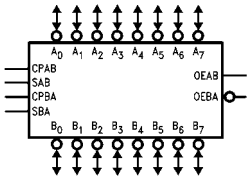

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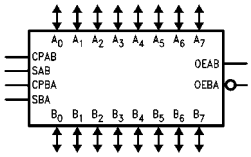

IEEE/IEC
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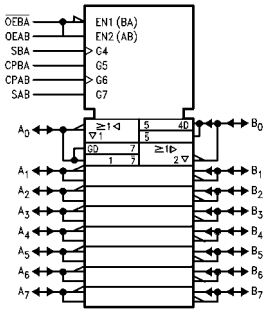
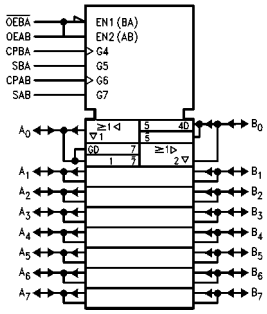


IEEE/IEC
74F652



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7, B_0–B_7	A and B Inputs/	1.0/1.0	20 µA/–0.6 mA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
CPAB, CPBA	Clock Inputs	1.0/1.0	20 µA/–0.6 mA
SAB, SBA	Select Inputs	1.0/1.0	20 µA/–0.6 mA
OEAB, $\overline{OEBA}$	Output Enable Inputs	1.0/1.0	20 µA/–0.6 mA

Function Table

Inputs						Inputs/Outputs (Note 1)		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	↑	↑	X	X			Store A and B Data
X	H	↑	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	↑	↑	X	X	Input	Output	Store A in Both Registers
L	X	H or L	↑	X	X	Not Specified	Input	Hold A, Store B
L	L	↑	↑	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level ↑ = LOW-to-HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or OEBA inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs.

Functional Description

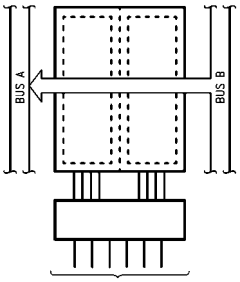
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in Figure 1 demonstrate the four fundamental bus-management functions that can be performed with the Octal bus transceivers and receivers.

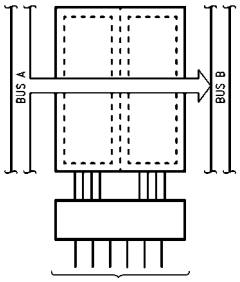
Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW-to-HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB and OEBA. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Note A: Real-Time Transfer Bus B to Bus A



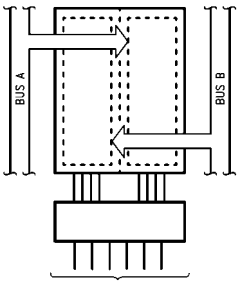
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Note B: Real-Time Transfer Bus A to Bus B



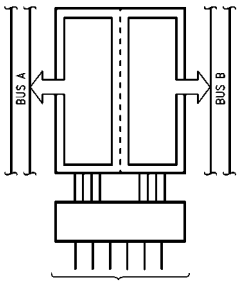
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

Note C: Storage



OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
X	H	⌐	X	X	X
L	X	X	⌐	X	X
L	H	⌐	⌐	X	X

Note D: Transfer Storage Data to A or B

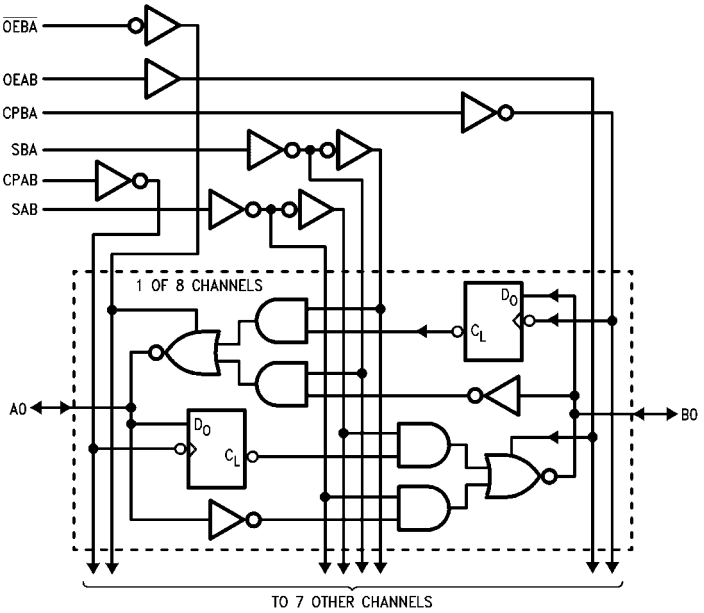


OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	X

FIGURE 1.

Logic Diagrams

74F652



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

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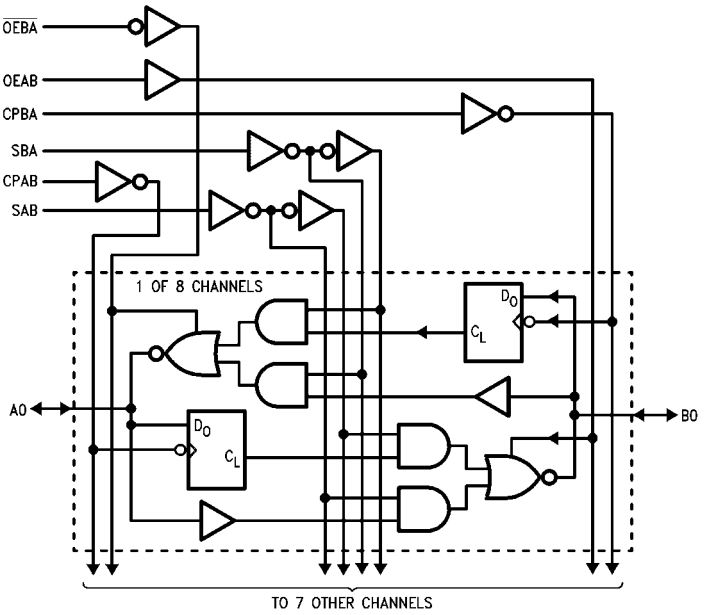


Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH Voltage 10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage 10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V (Non I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	VI_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		105	135	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		118	150	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		115	150	mA	Max	V_O = HIGH Z

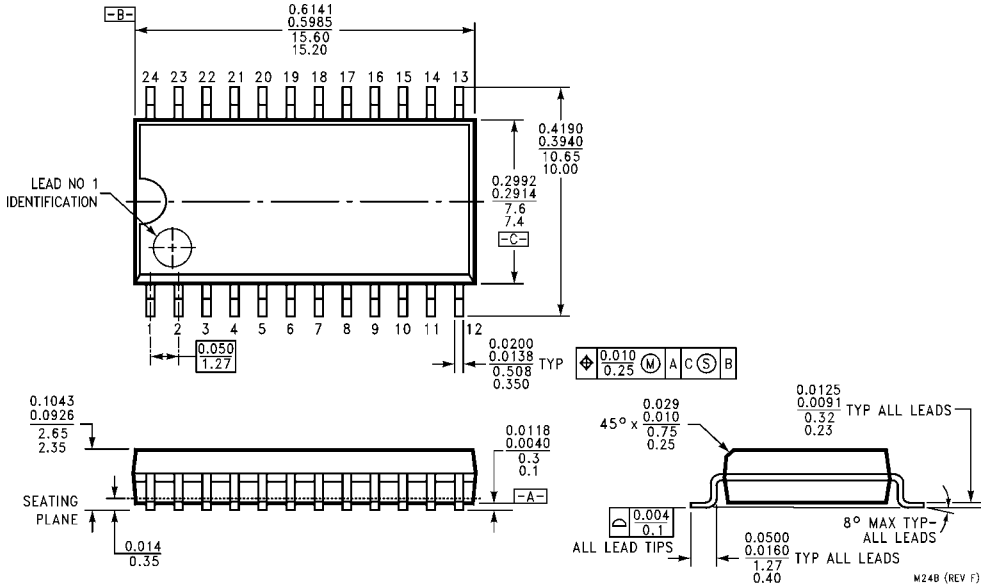
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Max. Clock Frequency	90		75		90		MHz
t_{PLH}	Propagation Delay	2.0	7.0	2.0	8.5	2.0	8.0	ns
t_{PHL}	Clock to Bus	2.0	8.0	2.0	9.5	2.0	9.0	
t_{PLH}	Propagation Delay	2.0	8.5	1.0	9.0	2.0	9.0	ns
t_{PHL}	Bus to Bus (74F651)	1.0	7.5	1.0	8.0	1.0	8.0	
t_{PLH}	Propagation Delay	1.0	7.0	1.0	8.0	1.0	7.5	ns
t_{PHL}	Bus to Bus (74F652)	1.0	6.5	1.0	8.0	1.0	7.0	
t_{PLH}	Propagation Delay	2.0	8.5	2.0	11.0	2.0	9.5	ns
t_{PHL}	SBA or SAB to A or B	2.0	8.0	2.0	10.0	2.0	9.0	

AC Operating Requirements

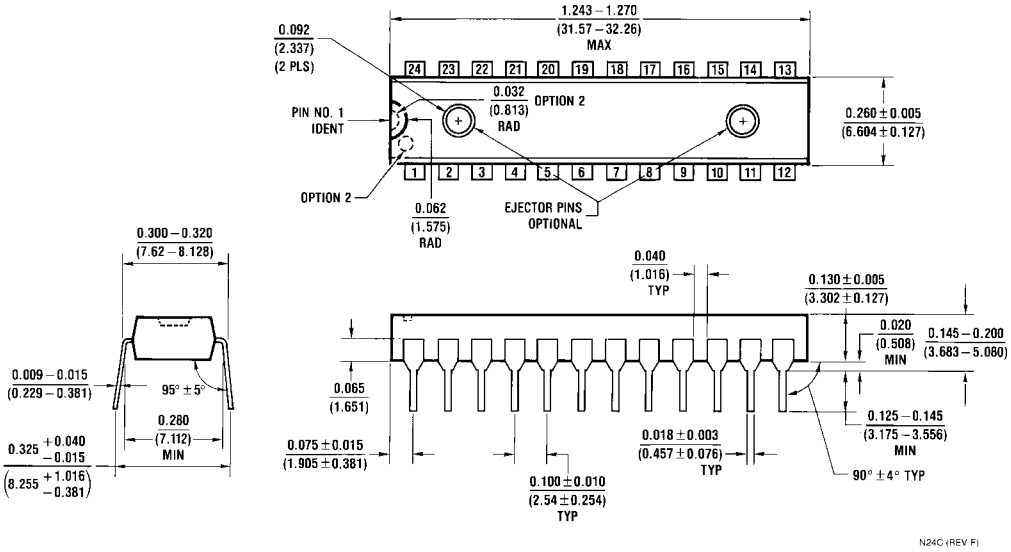
Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$ $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
t_{PZH}	Enable Time	2.0	9.5	2.0	10.0	2.0	10.0	ns
t_{PZL}	*OEBA to A	2.0	12.0	2.0	10.0	2.0	12.5	
t_{PHZ}	Disable Time	1.0	7.5	1.0	9.0	1.0	8.0	
t_{PLZ}	*OEBA to A	2.0	8.5	1.0	9.0	2.0	9.0	
t_{PZH}	Enable Time	2.0	9.5	2.0	10.0	2.0	10.0	
t_{PZL}	OEAB to B	3.0	13.0	2.0	12.0	3.0	14.0	
t_{PHZ}	Disable Time	2.0	9.0	1.0	9.0	2.0	10.0	ns
t_{PLZ}	OEAB to B	2.0	10.5	1.0	12.0	2.0	11.0	
$t_S(H)$	Setup Time, HIGH or	5.0		5.0		5.0		ns
$t_S(L)$	LOW, Bus to Clock	5.0		5.0		5.0		
$t_H(H)$	Hold Time, HIGH or	2.0		2.5		2.0		ns
$t_H(L)$	LOW, Bus to Clock	2.0		2.5		2.0		
$t_W(H)$	Clock Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

March 1988
Revised August 1999

74F657
Octal Bidirectional Transceiver with 8-Bit Parity Generator/Checker and 3-STATE Outputs

General Description

The 74F657 contains eight non-inverting buffers with 3-STATE outputs and an 8-bit parity generator/checker. It is intended for bus-oriented applications. The buffers have a guaranteed current sinking capability of 24 mA at the A Port and 64 mA at the B Port.

Features

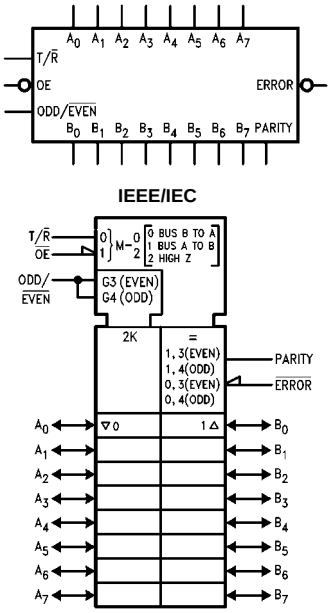
- 300 Mil 24-pin slimline DIP
- Combines 74F245 and 74F280A functions in one package
- 3-STATE outputs
- B Outputs sink 64 mA
- 12 mA source current, B side
- Input diodes for termination effects

Ordering Code:

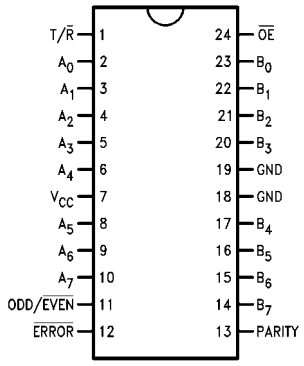
Order Number	Package Number	Package Description
75F657SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F657SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Data Inputs/	4.5/0.15	90 µA/– 90 µA
	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)
B_0–B_7	Data Inputs/	3.5/0.117	70 µA/–70 µA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
T/$\overline{R}$	Transmit/Receive Input	2.0/0.067	40 µA/–40 µA
$\overline{OE}$	Enable Input	2.0/0.067	40 µA/–40 µA
PARITY	Parity Input/	3.5/0.117	70 µA/–70µA
	3-STATE Output	600/106.6 (80)	–12 mA/64 mA (48 mA)
ODD/$\overline{EVEN}$	ODD/$\overline{EVEN}$ Parity Input	1.0/0.033	20 µA/–20 µA
$\overline{ERROR}$	Error Output	600/106.6 (80)	–12 mA/64 mA (48 mA)

Functional Description

The Transmit/Receive (T/$\overline{R}$) input determines the direction of the data flow through the bidirectional transceivers. Transmit (active HIGH) enables data from the A Port to the B Port; Receive (active LOW) enables data from the B Port to the A Port.

The Output Enable ($\overline{OE}$) input disables the parity and $\overline{ERROR}$ outputs and both the A and B Ports by placing them in a HIGH-Z condition when the Output Enable input is HIGH.

When transmitting (T/$\overline{R}$ HIGH), the parity generator detects whether an even or odd number of bits on the A Port are HIGH and compares these with the condition of the parity select (ODD/$\overline{EVEN}$). If the Parity Select is HIGH and an even number of A inputs are HIGH, the Parity output is HIGH.

In receiving mode (T/$\overline{R}$ LOW), the parity select and number of HIGH inputs on port B are compared to the condition of the Parity input. If an even number of bits on the B Port are HIGH, the parity select is HIGH, and the PARITY input is HIGH, then $\overline{ERROR}$ will be HIGH to indicate no error. If an odd number of bits on the B Port are HIGH, the parity select is HIGH, and the PARITY input is HIGH, the $\overline{ERROR}$ will be LOW indicating an error.

Function Table

Number of Inputs that are HIGH	Inputs			Input/ Output	Outputs	
	$\overline{OE}$	T/$\overline{R}$	ODD/$\overline{EVEN}$	Parity	$\overline{ERROR}$	Outputs Mode
0, 2, 4, 6, 8	L	H	H	H	Z	Transmit
	L	H	L	L	Z	Transmit
	L	L	H	H	H	Receive
	L	L	H	L	L	Receive
	L	L	L	H	L	Receive
	L	L	L	L	H	Receive
1, 3, 5, 7	L	H	H	L	Z	Transmit
	L	H	L	H	Z	Transmit
	L	L	H	H	L	Receive
	L	L	H	L	H	Receive
	L	L	L	H	H	Receive
	L	L	L	L	L	Receive
Immaterial	H	X	X	Z	Z	Z

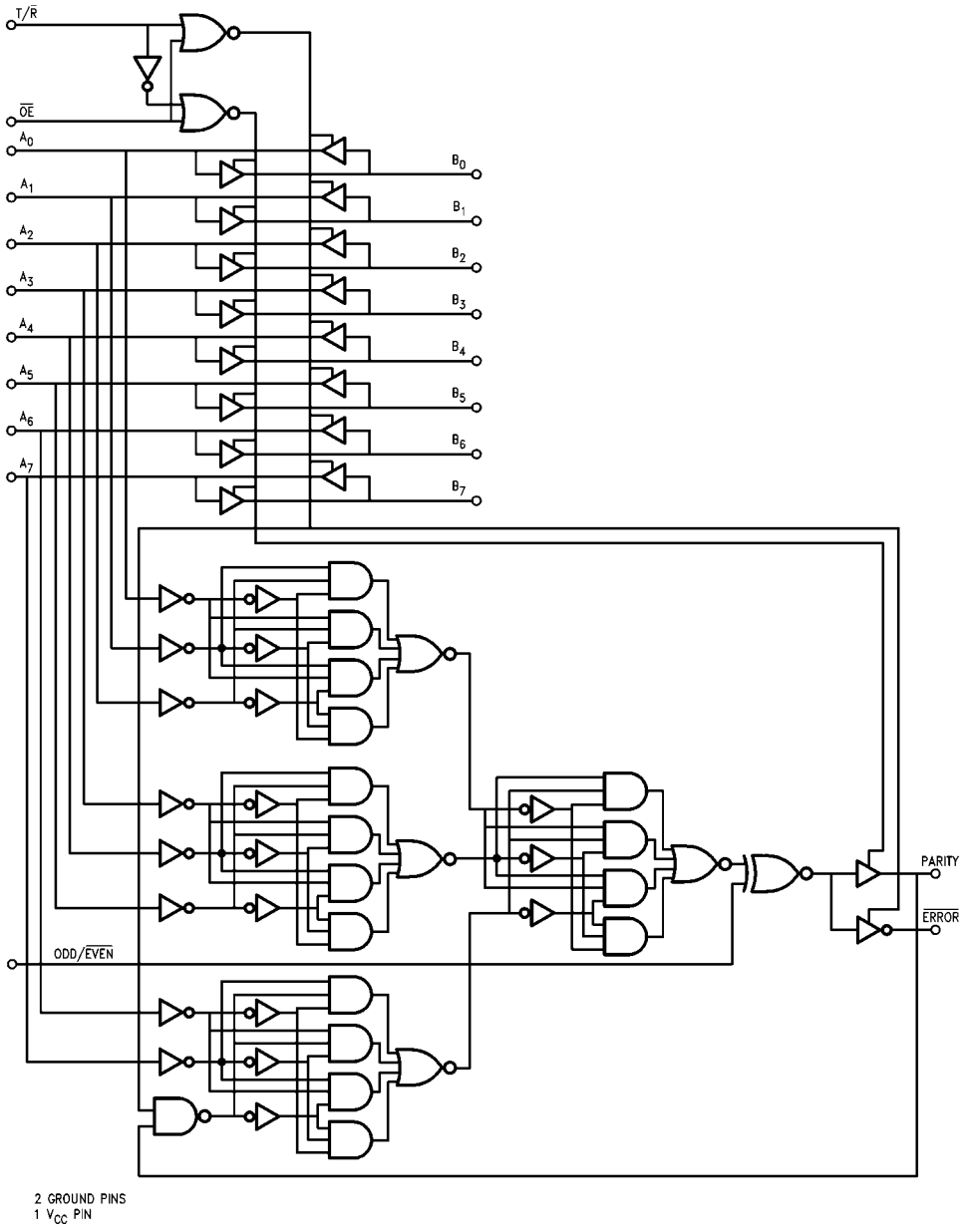
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Function Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

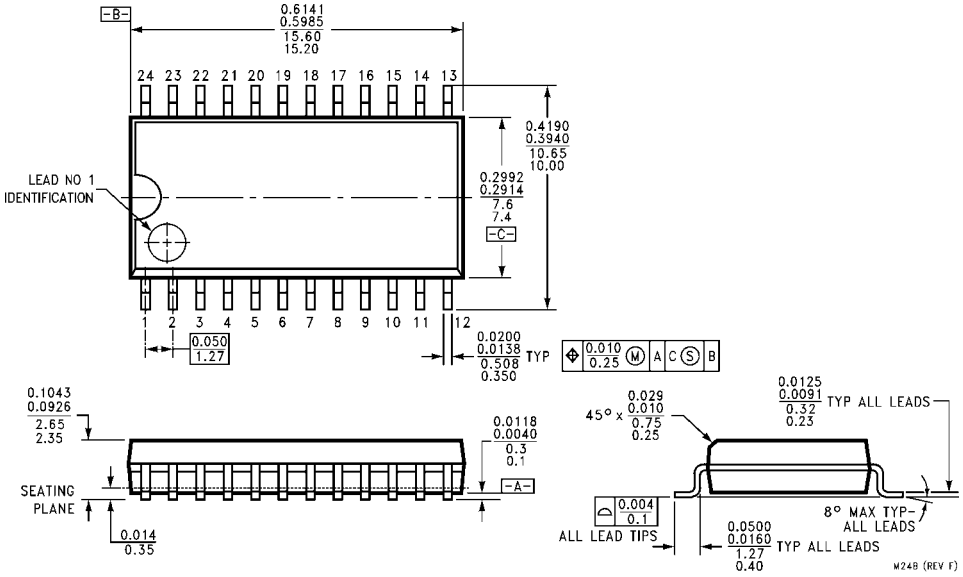
Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5					I_{OH} = −1 mA (A_n)
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA (A_n B_n, Parity, $\overline{ERROR}$)
		10% V_{CC}	2.0			V	Min	I_{OH} = −15 mA (B_n, Parity, $\overline{ERROR}$)
		5% V_{CC}	2.7					I_{OH} = −1 mA (A_n)
		5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n, Parity, $\overline{ERROR}$)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA (A_n)
	Voltage	10% V_{CC}			0.55			I_{OL} = 64 mA (B_n Parity, $\overline{ERROR}$)
I_{IH}	Input HIGH				20	µA	Max	V_{IN} = 2.7V (ODD/$\overline{EVEN}$)
	Current				40			V_{IN} 2.7V (T/$\overline{R}$, $\overline{OE}$)
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	V_{CC} = 0	V_{IN} = 7.0V (T/$\overline{R}$, $\overline{OE}$, ODD/$\overline{EVEN}$)
I_{BVIT}	Input HIGH Current				1.0	mA	Max	V_{IN} = 5.5V (Parity, B_n)
	Breakdown Test (I/O)				2.0			V_{IN} = 5.5V (A_n)
I_{IL}	Input LOW				−20	µA	Max	V_{IN} = 0.5V (ODD/$\overline{EVEN}$)
	Current				−40			V_{IN} = 0.5V (T/$\overline{R}$, $\overline{OE}$)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V ($\overline{ERROR}$)
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V ($\overline{ERROR}$)
I_{IH} + I_{OZH}	Output Leakage				70	µA	Max	$V_{I/O}$ = 2.7V (B_n, Parity)
	Current				90			$V_{I/O}$ = 2.7V (A_n)
I_{IL} + I_{OZL}	Output Leakage				−70	µA	Max	$V_{I/O}$ = 0.5V (B_n, Parity)
	Current				−90			$V_{I/O}$ = 0.5V (A_n)
I_{OS}	Output Short-Circuit		−60		−150	mA	Max	V_{OUT} = 0V (A_n)
	Current		−100		−225			V_{OUT} = 0V (B_n, Parity, $\overline{ERROR}$)
I_{CEX}	Output HIGH Leakage				250	µA	Max	V_{OUT} = V_{CC} ($\overline{ERROR}$)
	Current				1.0	mA	Max	V_{OUT} = V_{CC} (B_n, Parity)
					2.0	mA	Max	V_{OUT} = V_{CC} (A_n)
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V (A_n, B_n, Parity, $\overline{ERROR}$)
I_{CCH}	Power Supply Current			101	125	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			112	150	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			109	145	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.5	8.0	2.5	9.5	2.5	9.0	ns
t_{PHL}	A_n to B_n, B_n to A_n	3.0	4.9	7.5	3.0	8.5	3.0	8.0	
t_{PLH}	Propagation Delay	6.5	10.1	14.0	5.5	18.0	6.0	16.0	ns
t_{PHL}	A_n to Parity	7.0	10.9	15.0	5.5	20.5	6.0	16.5	
t_{PLH}	Propagation Delay	4.5	7.8	11.0	4.0	14.0	4.0	13.0	ns
t_{PHL}	ODD/$\overline{\text{EVEN}}$ to PARITY	4.5	8.8	12.0	4.5	16.5	4.5	13.5	
t_{PLH}	Propagation Delay	4.5	7.5	11.0	4.0	14.0	4.0	13.0	ns
t_{PHL}	ODD/$\overline{\text{EVEN}}$ to $\overline{\text{ERROR}}$	4.5	8.2	12.0	4.5	16.5	4.5	13.5	
t_{PLH}	Propagation Delay	8.0	14.0	20.5	7.5	27.0	7.5	23.0	ns
t_{PHL}	B_n to $\overline{\text{ERROR}}$	8.0	15.0	21.5	7.5	28.5	7.5	23.5	
t_{PLH}	Propagation Delay	7.0	10.8	15.5	6.0	20.0	6.0	17.0	ns
t_{PHL}	PARITY to $\overline{\text{ERROR}}$	7.5	11.8	16.5	6.5	22.0	7.5	18.5	
t_{PZH}	Output Enable Time	3.0	5.0	8.0	2.5	11.0	2.5	9.5	ns
t_{PZL}	$\overline{\text{OE}}$ to A_n/B_n	4.0	6.5	10.0	3.5	13.5	3.5	11.0	
t_{PHZ}	Output Disable Time	1.0	4.5	8.0	1.0	9.5	1.0	9.0	ns
t_{PLZ}	$\overline{\text{OE}}$ to A_n/B_n	1.0	4.9	7.5	1.0	8.5	1.0	8.0	
t_{PZH}	Output Enable Time	3.0	5.0	8.0	2.5	11.0	2.5	9.5	ns
t_{PZL}	$\overline{\text{OE}}$ to $\overline{\text{ERROR}}$ (Note 3)	4.0	7.7	10.0	3.5	13.5	3.5	11.0	
t_{PHZ}	Output Disable Time	1.0	4.5	8.0	1.0	9.5	1.0	9.0	ns
t_{PLZ}	$\overline{\text{OE}}$ to $\overline{\text{ERROR}}$	1.0	4.9	7.5	1.0	8.5	1.0	8.0	
t_{PZH}	Output Enable Time	3.0	5.0	8.0	2.5	11.0	2.5	9.5	ns
t_{PZL}	$\overline{\text{OE}}$ to PARITY	4.0	7.7	10.0	3.5	13.5	3.5	11.0	
t_{PHZ}	Output Disable Time	1.0	4.6	8.0	1.0	9.5	1.0	9.0	ns
t_{PLZ}	$\overline{\text{OE}}$ to PARITY	1.0	5.1	7.5	1.0	8.5	1.0	8.0	

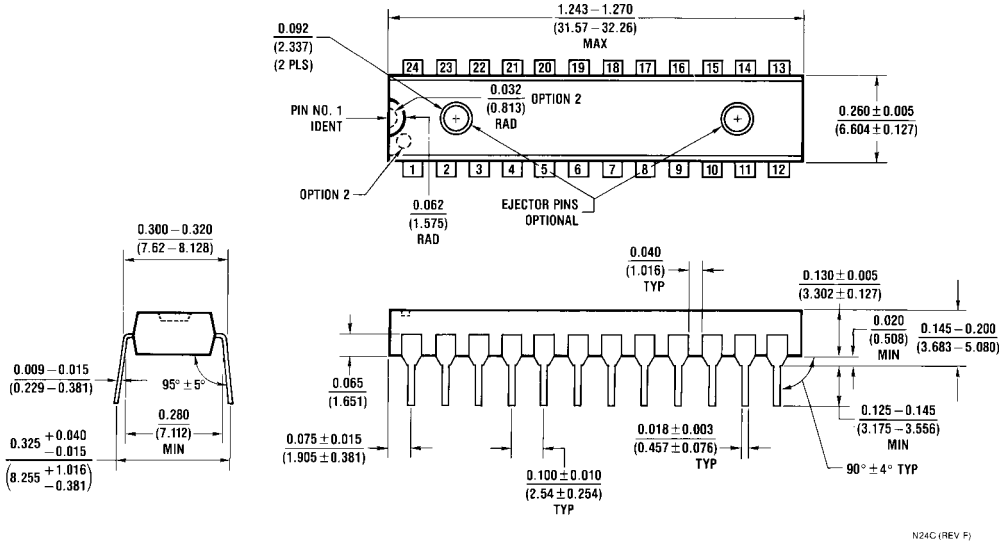
Note 3: These delay times reflect the 3-STATE recovery time only and not the signal time through the buffers or the parity check circuity. To assure VALID information at the $\overline{\text{ERROR}}$ pin, time must be allowed for the signal to propagate through the drivers (B to A), through the parity check circuitry (same as A to PARITY), and to the $\overline{\text{ERROR}}$ output after the $\overline{\text{ERROR}}$ pin has been enabled (Output Enable times). VALID data at the $\overline{\text{ERROR}}$ pin ≥ (A to PARITY) + (Output Enable Time).

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

April 1988
Revised August 1999

74F673A
16-Bit Serial-In, Serial/Parallel-Out Shift Register

General Description

The 74F673A contains a 16-bit serial-in, serial-out shift register and a 16-bit Parallel-Out storage register. A single pin serves either as an input for serial entry or as a 3-STATE serial output. In the Serial-Out mode, the data recirculates in the shift register. By means of a separate clock, the contents of the shift register are transferred to the storage register for parallel outputting. The contents of the storage register can also be parallel loaded back into the shift register. A HIGH signal on the Chip Select input prevents both shifting and parallel transfer. The storage register may be cleared via $\overline{STMR}$.

Features

- Serial-to-parallel converter
- 16-bit serial I/O shift register
- 16-bit parallel-out storage register
- Recirculating serial shifting
- Recirculating parallel transfer
- Common serial data I/O pin
- Slim 24 lead package

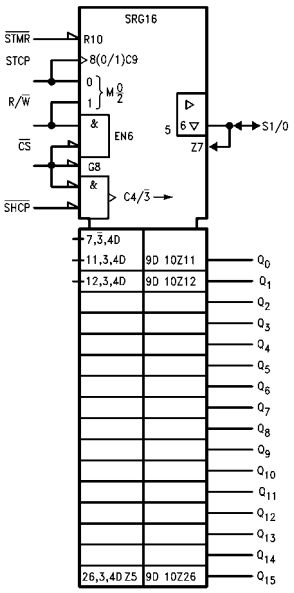
Ordering Code:

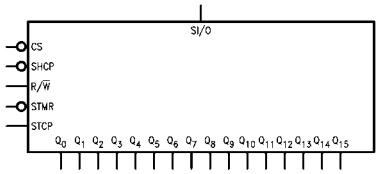
Order Number	Package Number	Package Description
74F673ASC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F673APC	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
74F673ASPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

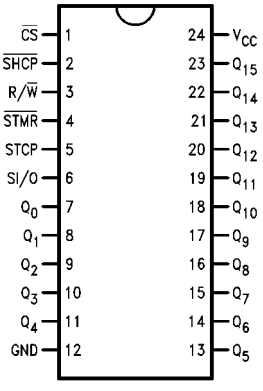
Logic Symbols

IEEE/IEC





Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{SHCP}$	Shift Clock Pulse Input (Active Falling Edge)	1.0/1.0	20 μA/–0.6 mA
$\overline{STMR}$	Store Master Reset Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
STCP	Store Clock Pulse Input	1.0/1.0	20 μA/–0.6 mA
R/$\overline{W}$	Read/Write Input	1.0/1.0	20 μA/–0.6 mA
SI/O	Serial Data Input or	3.5/1.0	70 μA/–0.6 mA
	3-STATE Serial Output	150/40	–3 mA/24 mA
Q_0–Q_{15}	Parallel Data Outputs	50/33.3	–1 mA/20 mA

Functional Description

The 16-bit shift register operates in one of four modes, as indicated in the Shift Register Operations Table. A HIGH signal on the Chip Select ($\overline{CS}$) input prevents clocking and forces the Serial Input/Output (SI/O) 3-STATE buffer into the high impedance state. During serial shift-out operations, the SI/O buffer is active (i.e., enabled) and the output data is also recirculated back into the shift register. When parallel loading the shift register from the storage register, serial shifting is inhibited.

The storage register has an asynchronous master reset ($\overline{STMR}$) input that overrides all other inputs and forces the Q_0–Q_{15} outputs LOW. The storage register is in the Hold mode when either $\overline{CS}$ or the Read/Write (R/$\overline{W}$) input is HIGH. With $\overline{CS}$ and R/$\overline{W}$ both LOW, the storage register is parallel loaded from the shift register.

Shift Register Operations Table

Control Inputs				SI/O	Operating Mode
$\overline{CS}$	R/$\overline{W}$	$\overline{SHCP}$	STCP	Status	
H	X	X	X	High Z	Hold
L	L		X	Data In	Serial Load
L	H	↓	L	Data Out	Serial Output with Recirculation
L	H	↓	H	Active	Parallel Load; No Shifting

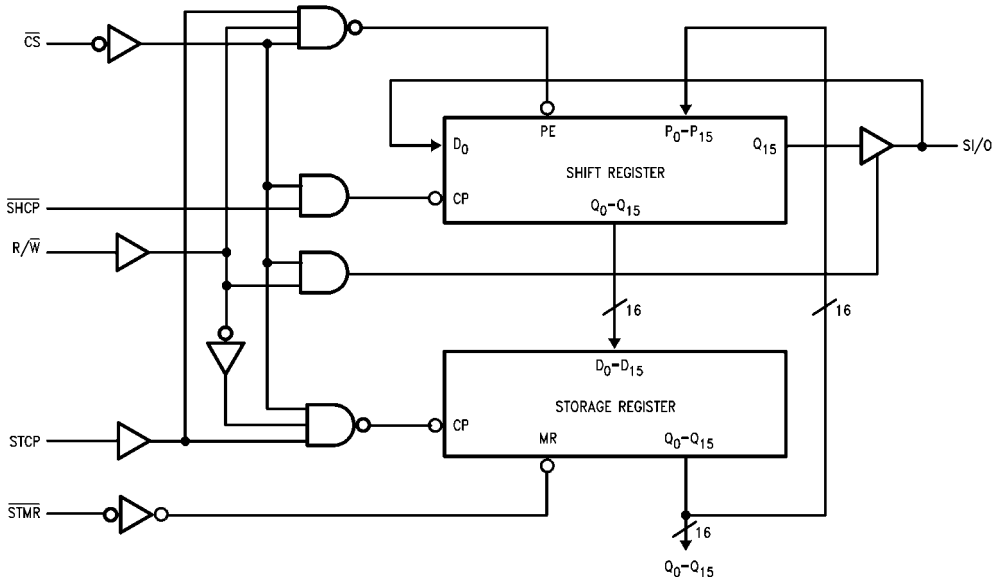
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↓ = HIGH-to-LOW Transition

Storage Register Operations Table

Control Inputs				Operating
$\overline{STMR}$	$\overline{CS}$	R/$\overline{W}$	STCP	Mode
L	X	X	X	Reset; Outputs LOW
H	H	X	X	Hold
H	X	H	X	Hold
H	L	L	↑	Parallel Load

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↑ = LOW-to-HIGH Transition

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA (Non I/O pins)
V_{OH}	Output HIGH	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA (Q_n, SI/O)
	Voltage	10% V_{CC}	2.4					I_{OH} = −3 mA (SI/O)
		5% V_{CC}	2.7					I_{OH} = −1 mA (Q_n, SI/O)
		5% V_{CC}	2.7					I_{OH} = −3 mA (SI/O)
V_{OL}	Output LOW	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA (Q_n)
	Voltage	10% V_{CC}			0.5			I_{OL} = 24 mA (SI/O)
I_{IH}	Input HIGH Current				20	µA	Max	V_{IN} = 2.7V (Non I/O pins)
I_{BVI}	Input HIGH Current Breakdown Test				100	µA	Max	V_{IN} = 7.0V (Non I/O pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)				1.0	mA	Max	V_{IN} = 5.5V (SI/O)
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{IH} + I_{OZH}	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (SI/O)
I_{IL} + I_{OZL}	Output Leakage Current				−650	µA	Max	V_{OUT} = 0.5V (SI/O)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			114	172	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			114	172	mA	Max	V_O = LOW

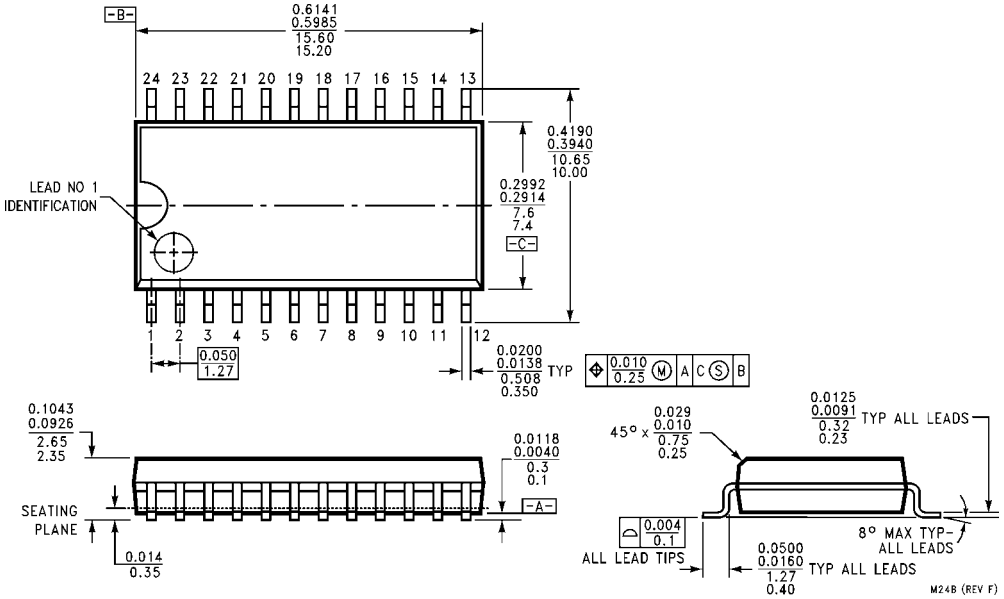
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	130		85		MHz
t_{PLH}	Propagation Delay	3.0	8.0	10.5	2.5	12.0	ns
t_{PHL}	STCP to Q_n	3.0	10.5	13.5	2.5	15.0	
t_{PHL}	Propagation Delay $\overline{STMR}$ to Q_n	6.0	16.5	20.5	5.5	22.5	ns
t_{PLH}	Propagation Delay	4.0	6.5	8.5	3.5	9.5	ns
t_{PHL}	$\overline{SHCP}$ to SI/O	4.5	8.0	10.5	4.0	12.0	
t_{PZH}	Output Enable Time	5.0	8.5	11.0	4.0	12.5	ns
t_{PZL}	$\overline{CS}$ to SI/O	5.5	9.0	11.5	4.5	13.0	
t_{PHZ}	Output Disable Time	3.5	5.5	7.5	3.0	8.5	
t_{PLZ}	$\overline{CS}$ to SI/O	3.0	4.5	6.5	2.5	7.5	
t_{PZH}	Output Enable Time	4.5	7.5	9.5	4.0	10.5	ns
t_{PZL}	R/$\overline{W}$ to SI/O	4.5	8.0	10.0	4.0	11.5	
t_{PHZ}	Output Disable Time	3.0	5.5	7.0	2.5	8.0	
t_{PLZ}	R/$\overline{W}$ to SI/O	2.5	4.0	5.5	2.0	6.5	

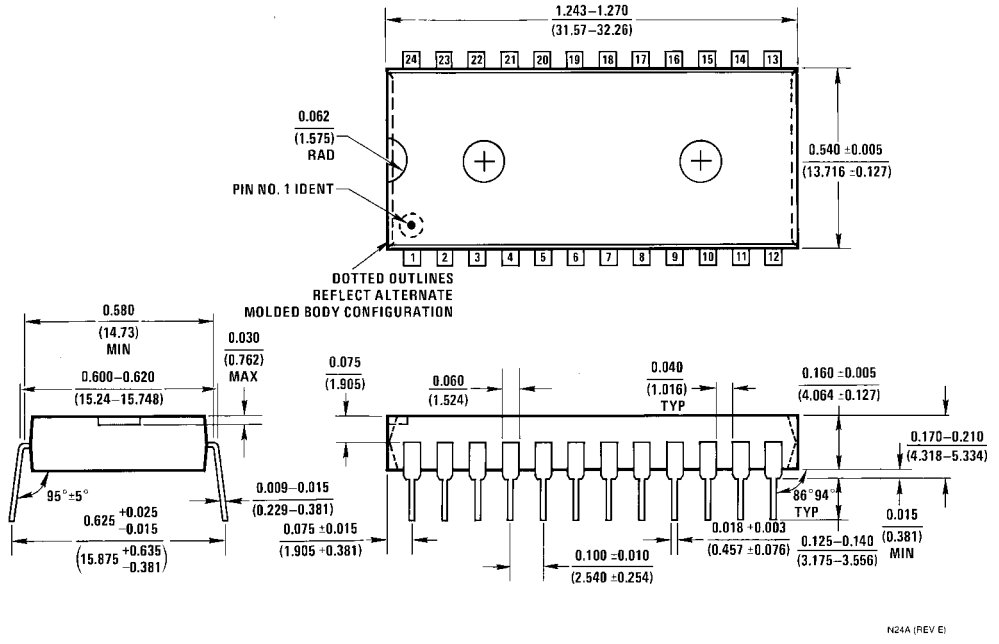
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.5		4.0		ns
$t_S(L)$	$\overline{CS}$ or R/$\overline{W}$ to STCP	6.0		7.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	$\overline{CS}$ or R/$\overline{W}$ to STCP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.5		ns
$t_S(L)$	SI/O to $\overline{SHCP}$	3.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.5		
$t_H(L)$	SI/O to $\overline{SHCP}$	3.0		3.5		

Physical Dimensions inches (millimeters) unless otherwise noted

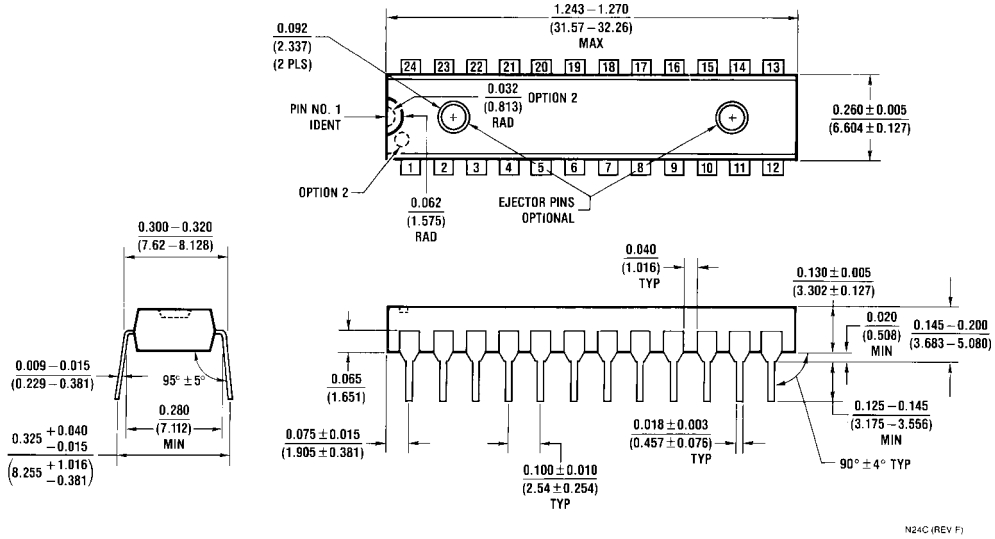


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
Package Number N24A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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April 1988
Revised August 1999

74F675A
16-Bit Serial-In, Serial/Parallel-Out Shift Register

General Description

The 74F675A contains a 16-bit serial in/serial out shift register and a 16-bit parallel out storage register. Separate serial input and output pins are provided for expansion to longer words. By means of a separate clock, the contents of the shift register are transferred to the storage register. The contents of the storage register can also be loaded back into the shift register. A HIGH signal on the Chip Select input prevents both shifting and parallel loading.

Features

- Serial-to-parallel converter
- 16-Bit serial I/O shift register
- 16-Bit parallel out storage register
- Recirculating parallel transfer
- Expandable for longer words
- Slim 24 lead package
- 74F675A version prevents false clocking through $\overline{CS}$ or R/$\overline{W}$ inputs

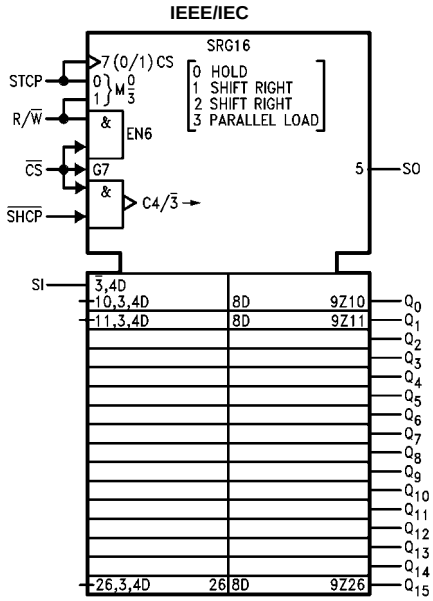
Ordering Code:

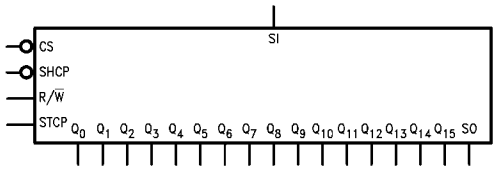
Order Number	Package Number	Package Description
74F675ASC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F675APC	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
74F675ASPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

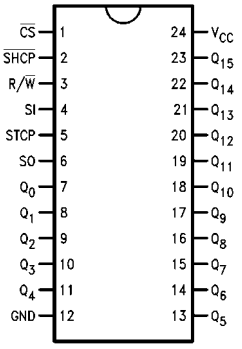
Logic Symbols

IEEE/IEC





Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
SI	Serial Data Input	1.0/1.0	20 µA/–0.6 mA
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/1.0	20 µA/–0.6 mA
$\overline{SHCP}$	Shift Clock Pulse Input (Active Falling Edge)	1.0/1.0	20 µA/–0.6 mA
STCP	Store Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
R/$\overline{W}$	Read/Write Input	1.0/1.0	20 µA/–0.6 mA
SO	Serial Data Output	50/33.3	–1 mA/20 mA
Q_0–Q_{15}	Parallel Data Outputs	50/33.3	–1 mA/20 mA

Functional Description

The 16-Bit shift register operates in one of four modes, as determined by the signals applied to the Chip Select ($\overline{CS}$), Read/Write (R/$\overline{W}$) and Store Clock Pulse (STCP) input. State changes are indicated by the falling edge of the Shift Clock Pulse ($\overline{SHCP}$). In the Shift Right mode, data enters D_0 from the Serial Input (SI) pin and exits from Q_{15} via the Serial Data Output (SO) pin. In the Parallel Load mode, data from the storage register outputs enter the shift register and serial shifting is inhibited.

The storage register is in the Hold mode when either $\overline{CS}$ or R/$\overline{W}$ is HIGH. With $\overline{CS}$ and R/$\overline{W}$ both LOW, the storage register is parallel loaded from the shift register on the rising edge of STCP.

To prevent false clocking of the shift register, $\overline{SHCP}$ should be in the LOW state during a LOW-to-HIGH transition of $\overline{CS}$. To prevent false clocking of the storage register, STCP should be LOW during a HIGH-to-LOW transition of $\overline{CS}$ if R/$\overline{W}$ is LOW, and should also be LOW during a HIGH-to-LOW transition of R/$\overline{W}$ if $\overline{CS}$ is LOW.

Shift Register Operations Table

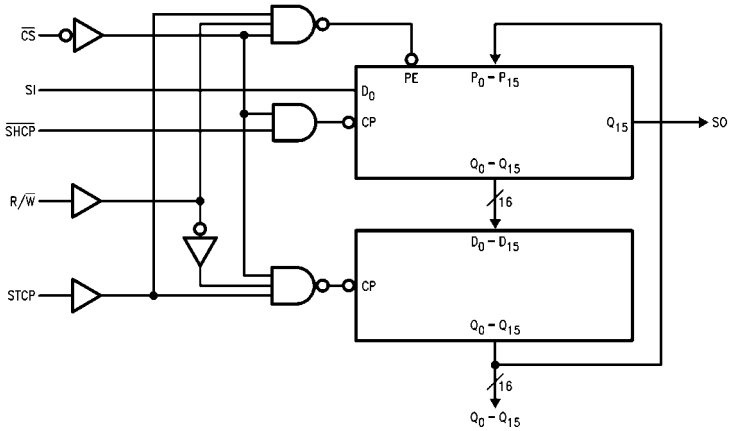
Control Inputs				Operating Mode
$\overline{CS}$	R/$\overline{W}$	$\overline{SHCP}$	STCP	
H	X	X	X	Hold
L	L	↘	X	Shift Right
L	H	↘	L	Shift Right
L	H	↘	H	Parallel Load, No Shifting

Storage Register Operations Table

Inputs			Operating Mode
$\overline{CS}$	R/$\overline{W}$	STCP	
H	X	X	Hold
L	H	X	Hold
L	L	↗	Parallel Load

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↘ = HIGH-to-LOW Transition
↗ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			106	160	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			106	160	mA	Max	V_O = LOW

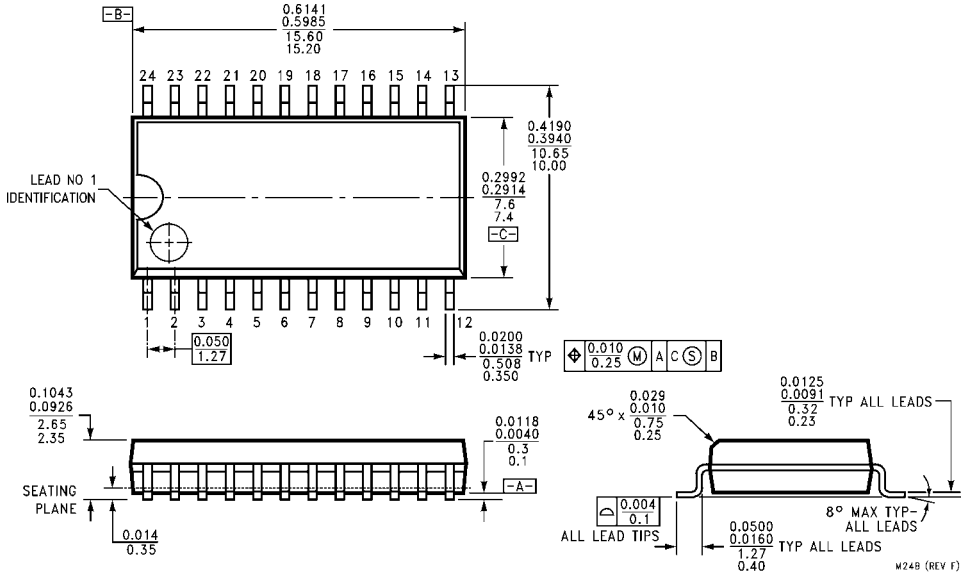
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	130		85		MHz
t_{PLH}	Propagation Delay	3.0	8.0	10.5	2.5	12.0	ns
t_{PHL}	STCP to Q_n	3.0	10.5	13.5	2.5	15.0	
t_{PLH}	Propagation Delay	4.0	7.0	9.5	3.5	10.5	ns
t_{PHL}	$\overline{SHCP}$ to SO	4.5	8.0	10.5	4.0	12.0	

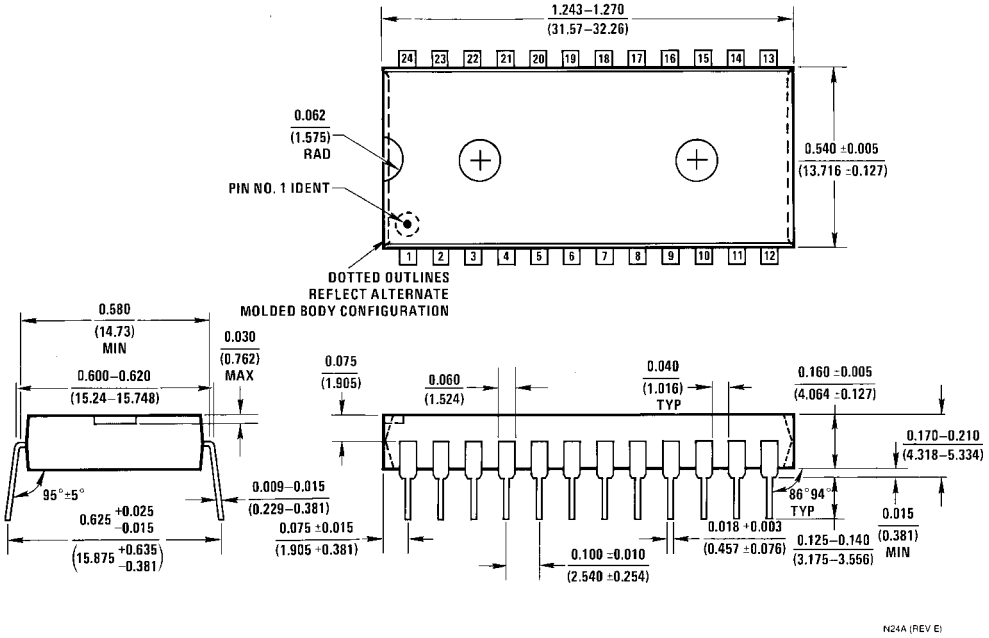
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	3.5		4.0		ns
$t_S(L)$	$\overline{CS}$ or R/$\overline{W}$ to STCP	5.5		6.5		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	$\overline{CS}$ or R/$\overline{W}$ to STCP	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.5		ns
$t_S(L)$	SI to $\overline{SHCP}$	3.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.5		
$t_H(L)$	SI to $\overline{SHCP}$	3.0		3.5		
$t_S(H)$	Setup Time, HIGH or LOW	6.5		7.5		ns
$t_S(L)$	R/$\overline{W}$ to $\overline{SHCP}$	9.0		10.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	R/$\overline{W}$ to $\overline{SHCP}$	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	7.0		8.0		ns
$t_S(L)$	STCP to $\overline{SHCP}$	7.0		8.0		
$t_H(H)$	Hold Time, HIGH or LOW	0		0		
$t_H(L)$	STCP to $\overline{SHCP}$	0		0		
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.5		ns
$t_S(L)$	$\overline{CS}$ to $\overline{SHCP}$	3.0		3.5		
$t_H(H)$	Hold Time, HIGH or LOW	3.0		3.5		
$t_H(L)$	$\overline{CS}$ to $\overline{SHCP}$	3.0		3.5		
$t_W(H)$	$\overline{SHCP}$ Pulse Width	5.0		6.0		ns
$t_W(L)$	HIGH or LOW	5.0		6.0		
$t_W(H)$	STCP Pulse Width	6.0		7.0		
$t_W(L)$	HIGH or LOW	5.0		6.0		
$t_S(L)$	$\overline{SHCP}$ to STCP	8.0		9.0		ns
$t_H(H)$	$\overline{SHCP}$ to STCP	0.0		0.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

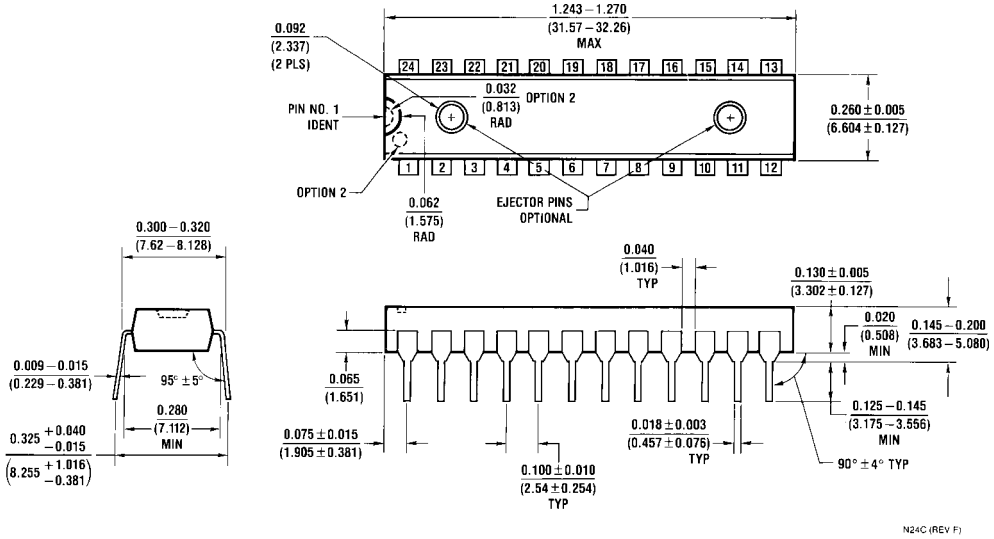


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
Package Number N24A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F676
16-Bit Serial/Parallel-In, Serial-Out Shift Register

General Description

The 74F676 contains 16 flip-flops with provision for synchronous parallel or serial entry and serial output. When the Mode (M) input is HIGH, information present on the parallel data (P_0–P_{15}) inputs is entered on the falling edge of the Clock Pulse ($\overline{CP}$) input signal. When M is LOW, data is shifted out of the most significant bit position while information present on the Serial (SI) input shifts into the least significant bit position. A HIGH signal on the Chip Select ($\overline{CS}$) input prevents both parallel and serial operations.

Features

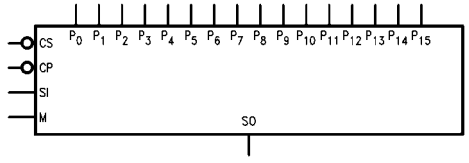
- 16-bit parallel-to-serial conversion
- 16-bit serial-in, serial-out
- Chip select control
- Slim 24 lead 300 mil package

Ordering Code:

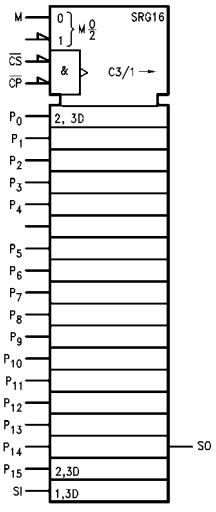
Order Number	Package Number	Package Description
74F676SC	M24B	28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F676PC	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
74F676SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

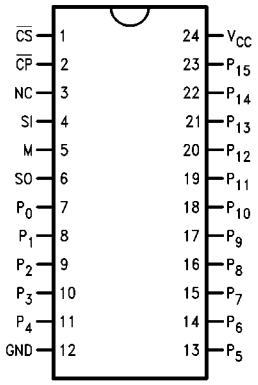
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
P_0–P_{15}	Parallel Data Inputs	1.0/1.0	20 μA/–0.6 mA
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
$\overline{CP}$	Clock Pulse Input (Active LOW)	1.0/1.0	20 μA/–0.6 mA
M	Mode Select Input	1.0/1.0	20 μA/–0.6 mA
SI	Serial Data Input	1.0/1.0	20 μA/–0.6 mA
SO	Serial Output	50/33.3	–1 mA/20 mA

Functional Description

The 16-bit shift register operates in one of three modes, as indicated in the Shift Register Operations Table.

HOLD— a HIGH signal on the Chip Select ($\overline{CS}$) input prevents clocking, and data is stored in the sixteen registers.

Shift/Serial Load— data present on the SI pin shifts into the register on the falling edge of $\overline{CP}$. Data enters the Q_0 position and shifts toward Q_{15} on successive clocks, finally appearing on the SO pin.

Parallel Load— data present on P_0–P_{15} are entered into the register on the falling edge of $\overline{CP}$. The SO output represents the Q_{15} register output.

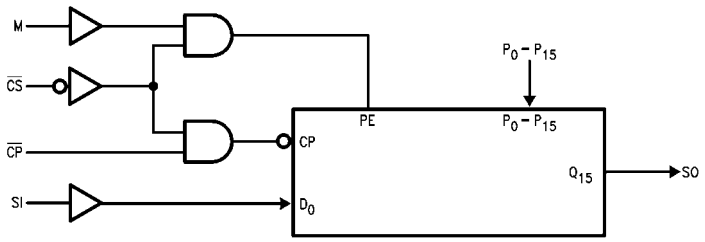
To prevent false clocking, $\overline{CP}$ must be LOW during a LOW-to-HIGH transition of $\overline{CS}$.

Shift Register Operations Table

Control Input			Operating Mode
$\overline{CS}$	M	$\overline{CP}$	
H	X	X	Hold
L	L	⌐	Shift/Serial Load
L	H	⌐	Parallel Load

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = HIGH-to-LOW Transition

Block Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current				72	mA	Max	

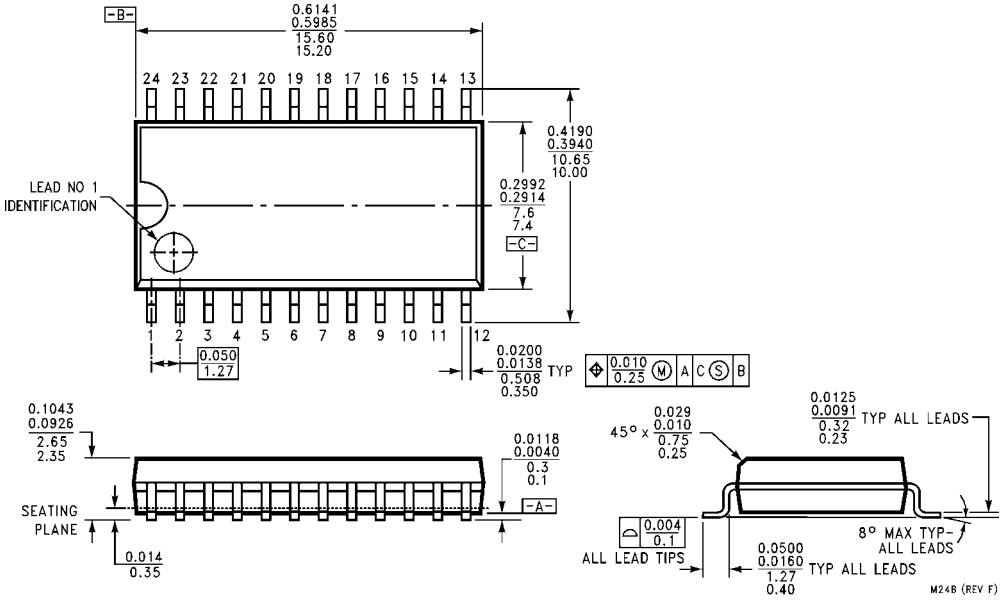
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	110		45		90		MHz
t_{PLH}	Propagation Delay	4.5	9.0	11.0	4.5	17.0	4.5	12.0	ns
t_{PHL}	$\overline{CP}$ to SO	5.0	9.0	12.5	5.0	14.5	5.0	13.5	

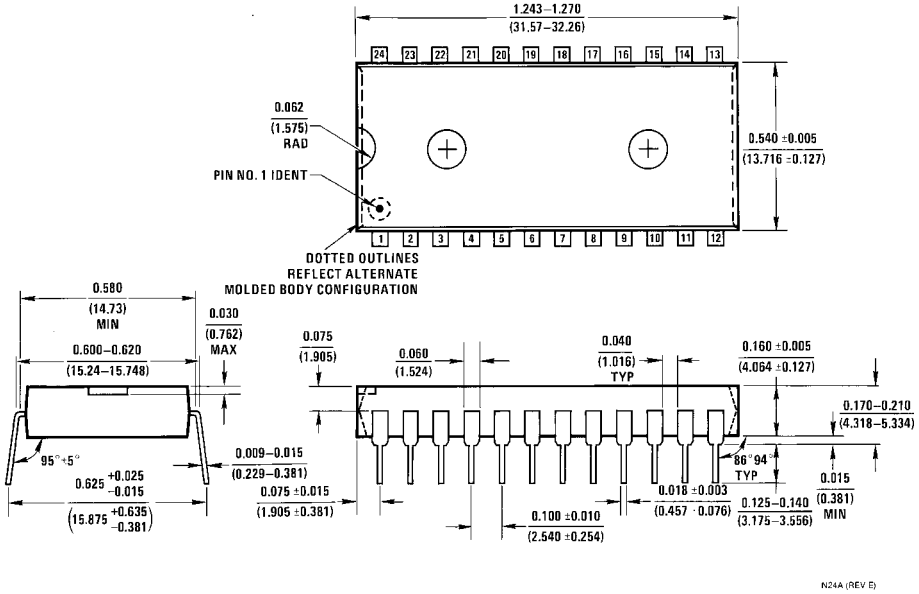
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $125°C$, $V_{CC} = +5.0V$		T_A, V_{CC} = ____, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	4.0		4.0		4.0		ns
$t_S(L)$	SI to $\overline{CP}$	4.0		4.0		4.0		
$t_H(H)$	Hold Time, HIGH or LOW	4.0		4.0		4.0		
$t_H(L)$	SI to $\overline{CP}$	4.0		4.0		4.0		
$t_S(H)$	Setup Time, HIGH or LOW	3.0		3.0		3.0		ns
$t_S(L)$	P_n to $\overline{CP}$	3.0		3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	4.0		4.0		4.0		
$t_H(L)$	P_n to $\overline{CP}$	4.0		4.0		4.0		
$t_S(H)$	Setup Time, HIGH or LOW	8.0		8.0		8.0		ns
$t_S(L)$	M to $\overline{CP}$	8.0		8.0		8.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.0		2.0		
$t_H(L)$	M to $\overline{CP}$	2.0		2.0		2.0		
$t_S(L)$	Setup Time, LOW $\overline{CS}$ to $\overline{CP}$	10.0		12.0		10.0		ns
$t_H(H)$	Hold Time, HIGH $\overline{CS}$ to $\overline{CP}$	10.0		10.0		10.0		
$t_W(H)$	$\overline{CP}$ Pulse Width	4.0		5.0		4.0		ns
$t_W(L)$	HIGH or LOW	6.0		9.0		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted

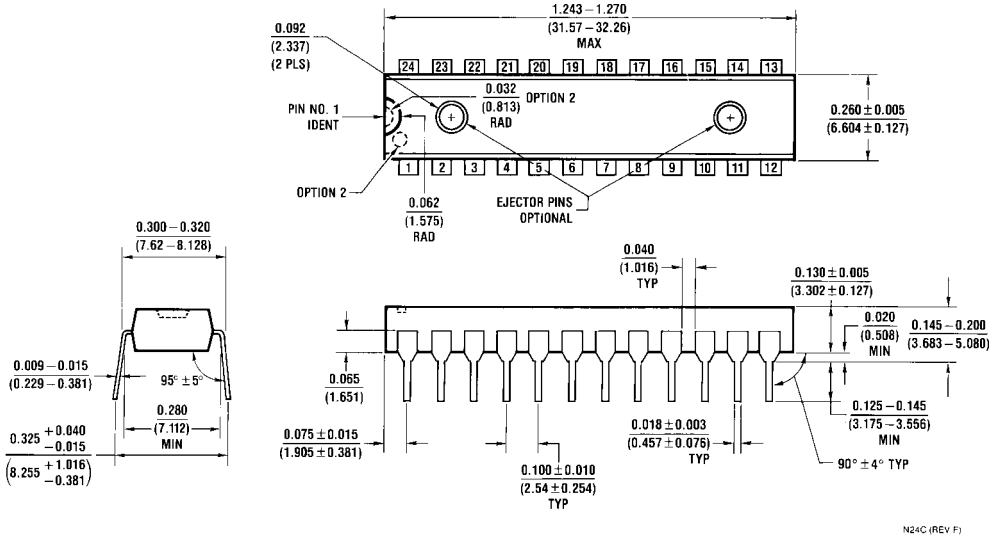


28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-010, 0.600 Wide
Package Number N24A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F74
Dual D-Type Positive Edge-Triggered Flip-Flop

General Description

The F74 is a dual D-type flip-flop with Direct Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. Clock triggering occurs at a voltage level of the clock pulse and is not directly related to the transition time of the positive-going pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ sets Q to HIGH level

LOW input to $\overline{C}_D$ sets Q to LOW level

Clear and Set are independent of clock

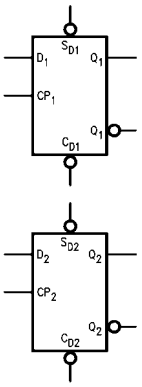
Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Ordering Code:

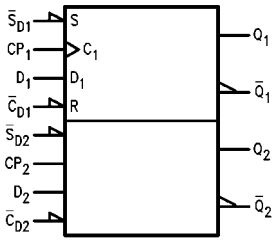
Order Number	Package Number	Package Description
74F74SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F74PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

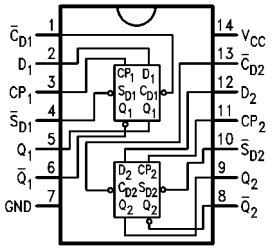
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

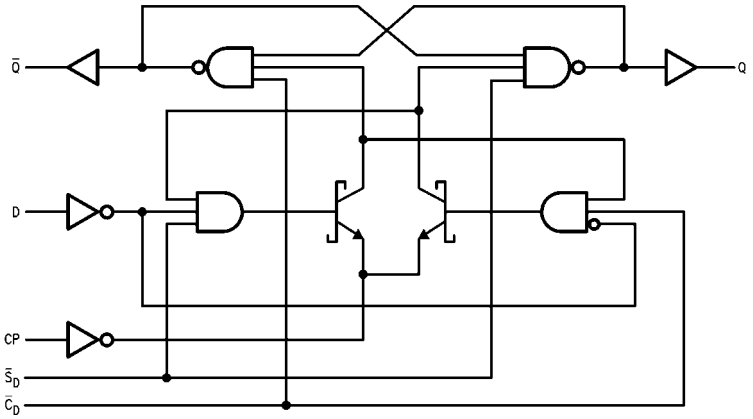
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_1, D_2	Data Inputs	1.0/1.0	20 µA/–0.6 mA
CP_1, CP_2	Clock Pulse Inputs (Active Rising Edge)	1.0/1.0	20 µA/–0.6 mA
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs (Active LOW)	1.0/3.0	20 µA/–1.8 mA
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs (Active LOW)	1.0/3.0	20 µA/–1.8 mA
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs	50/33.3	–1 mA/20 mA

Truth Table

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	⌐	h	H	L
H	H	⌐	l	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H (h) = HIGH Voltage Level
L (l) = LOW Voltage Level
X = Immaterial
Q_0 = Previous Q ($\overline{Q}$) before LOW-to-HIGH Clock Transition
Lower case letters indicate the state of the referenced input or output one setup time prior to the LOW-to-HIGH clock transition.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V (D, CP)
					−1.8			V_{IN} = 0.5V ($\overline{C}_D$, $\overline{S}_D$)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CC}	Power Supply Current			10.5	16.0	mA	Max	

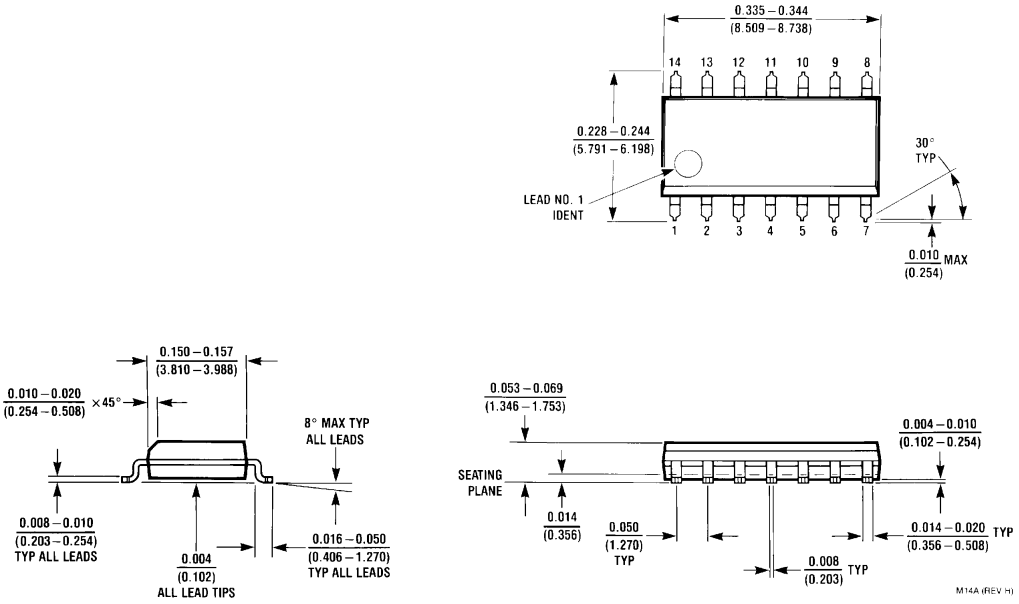
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	125		100		MHz
t_{PLH}	Propagation Delay	3.8	5.3	6.8	3.8	7.8	ns
t_{PHL}	CP_n to Q_n or $\overline{Q}_n$	4.4	6.2	8.0	4.4	9.2	
t_{PLH}	Propagation Delay	3.2	4.6	6.1	3.2	7.1	ns
t_{PHL}	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	3.5	7.0	9.0	3.5	10.5	

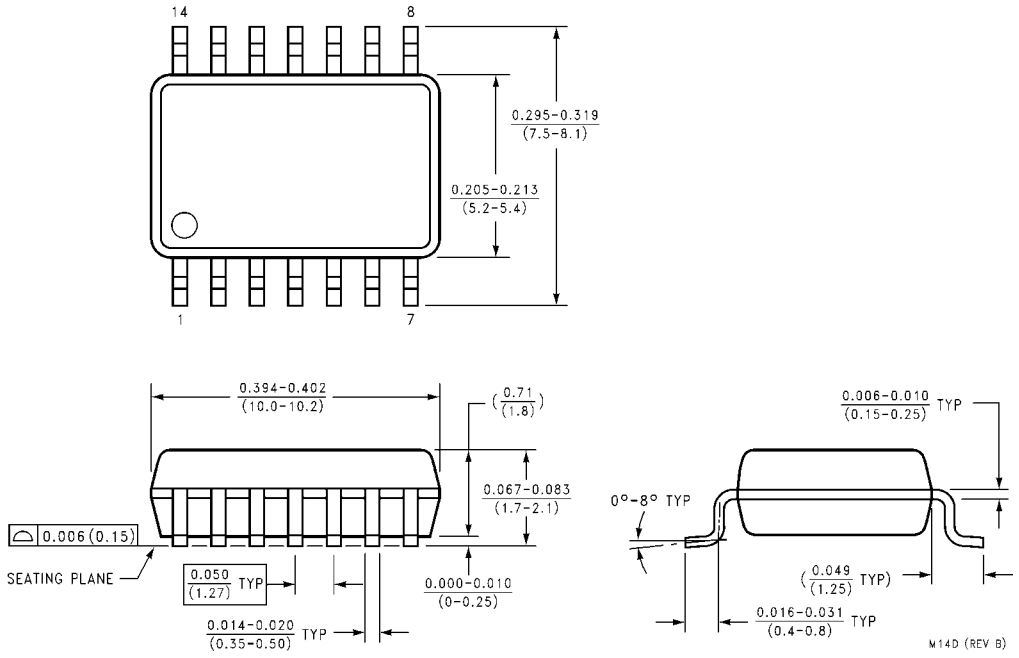
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.0		ns
$t_S(L)$	D_n to CP_n	3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.0		1.0		
$t_H(L)$	D_n to CP_n	1.0		1.0		
$t_W(H)$	CP_n Pulse Width	4.0		4.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		
$t_W(L)$	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ Pulse Width LOW	4.0		4.0		ns
t_{REC}	Recovery Time $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to CP	2.0		2.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted

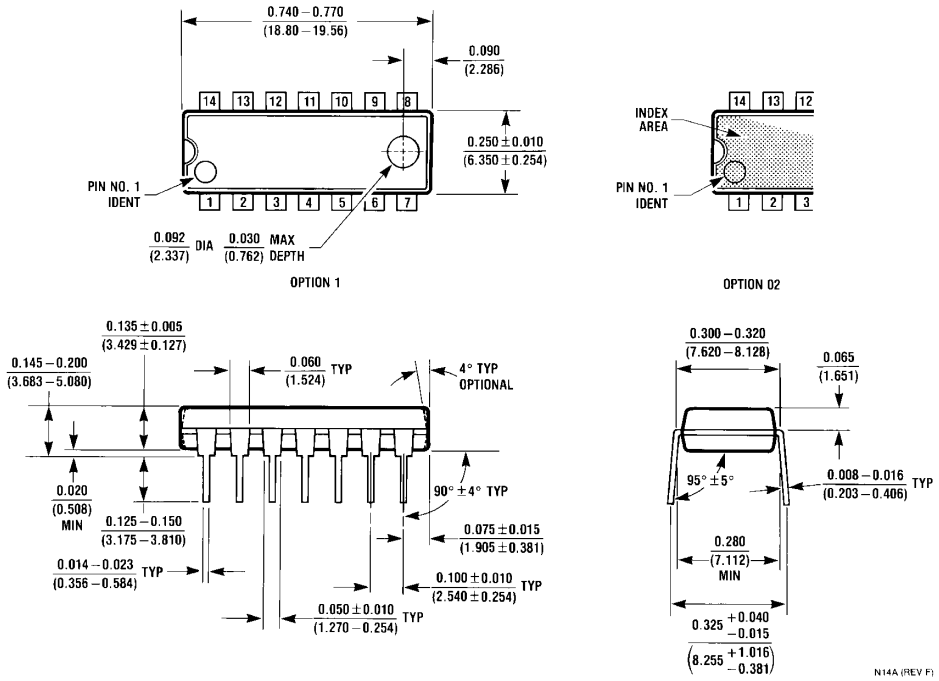


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F779
8-Bit Bidirectional Binary Counter with 3-STATE Outputs

General Description

The 74F779 is a fully synchronous 8-stage up/down counter with multiplexed 3-STATE I/O ports for bus-oriented applications. All control functions (hold, count up, count down, synchronous load) are controlled by two mode pins (S_0, S_1). The device also features carry lookahead for easy cascading. All state changes are initiated by the rising edge of the clock.

Features

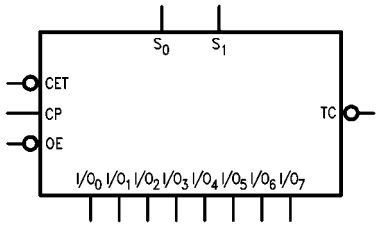
- Multiplexed 3-STATE I/O ports
- Built-in lookahead carry capability
- Count frequency 100 MHz typ
- Supply current 80 mA typ
- Available in SOIC (300 mil only)

Ordering Code:

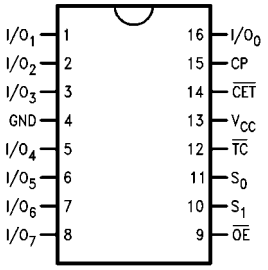
Order Number	Package Number	Package Description
74F779SC	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F779PC	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

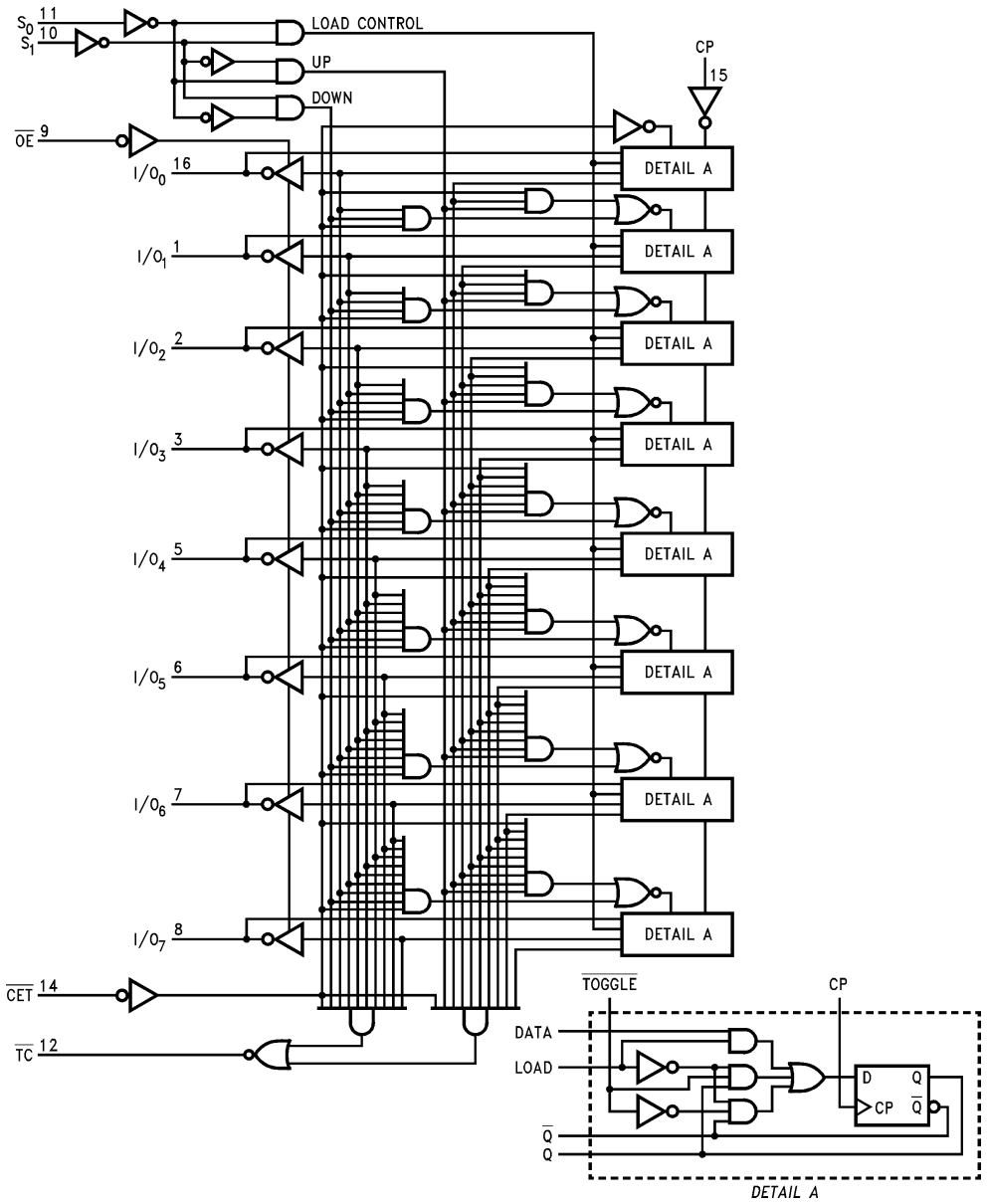
Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
I/O_0–I/O_7	Data Inputs	0.25/0.33	5 µA/–0.2 mA
	Data Outputs	75/15 (12.5)	–3 mA/24 mA (20 mA)
S_0, S_1	Select Inputs	0.25/0.33	5 µA/–0.2 mA
$\overline{OE}$	Output Enable Input (Active LOW)	0.25/0.33	5 µA/–0.2 mA
$\overline{CET}$	Count Enable Trickle Input (Active LOW)	0.25/0.33	5 µA/–0.2 mA
CP	Clock Pulse Input (Active Rising Edge)	0.25/0.33	5 µA/–0.2 mA
$\overline{TC}$	Terminal Count Output (Active LOW)	25/12.5	–1 mA/20 mA

Function Table

S_1	S_0	$\overline{CET}$	$\overline{OE}$	CP	Function
X	X	X	H	X	I/O_0 to I/O_7 in High Z
X	X	X	L	X	Flip-Flop Outputs Appear on I/O Lines
L	L	X	H	⌐	Parallel Load All Flip-Flops
(Not LL)		H	X	⌐	Hold ($\overline{TC}$ Held HIGH)
H	H	X	X	⌐	Hold
H	L	L	X	⌐	Count Up
L	H	L	X	⌐	Count Down

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level ⌐ = LOW-to-HIGH Clock Transition
(Not LL) means S_0 and S_1 should never both be LOW level at the same time.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current ((Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		5% V_{CC}	2.7					
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 20 mA
		5% V_{CC}			0.5			I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V (Non-I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (Non-I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (I/O_n)
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{ZZ}	Bus Drainage Test				500	µA	0.0	V_{OUT} = 5.25V
I_{IL}	Input LOW Current				−0.2	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
$I_{IH} + I_{OZH}$	Output Leakage Current				70	µA	Max	V_{OUT} = 2.7V (I/O_n)
$I_{IL} + I_{OZL}$	Output Leakage Current				−200	µA	Max	V_{OUT} = 0.5V (I/O_n)
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current				90	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current				105	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current				110	mA	Max	V_O = HIGH Z

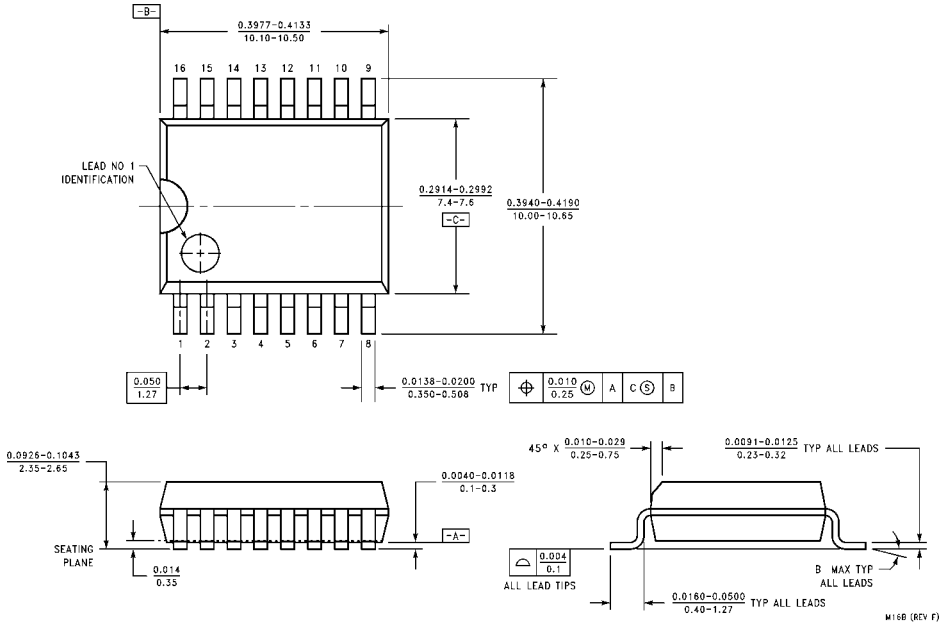
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	105		90		
t_{PLH}	Propagation Delay	3.0	5.0	8.0	3.0	8.5	ns
t_{PHL}	CP to I/O_n	5.0	7.5	11.0	5.0	11.0	
t_{PLH}	Propagation Delay	5.0	7.5	9.0	5.0	10.0	ns
t_{PHL}	CP to $\overline{TC}$	5.0	9.3	10.5	5.0	11.5	
t_{PLH}	Propagation Delay	2.5	3.8	5.5	2.5	6.0	ns
t_{PHL}	$\overline{CET}$ to $\overline{TC}$	4.5	6.1	8.0	4.5	8.5	
t_{PLH}	Propagation Delay	3.5	6.5	12.0	3.5	13.0	ns
t_{PHL}	SN to $\overline{TC}$	3.5	7.5	12.0	3.5	13.0	
t_{PZH}	Output Enable Time	3.0	5.0	7.0	3.0	8.0	ns
t_{PZL}	$\overline{OE}$ to I/O_n	5.0	8.0	10.0	5.0	10.5	
t_{PHZ}	Output Disable Time	1.0	4.0	6.5	1.0	7.0	ns
t_{PLZ}	$\overline{OE}$ to I/O_n	1.0	3.7	6.5	1.0	7.0	

AC Operating Requirements

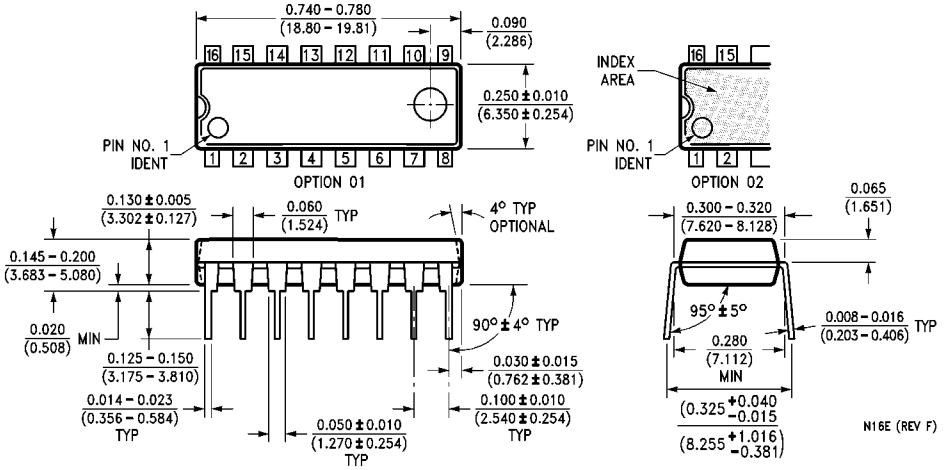
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time	5.0		5.0		ns
$t_S(L)$	I/O_n to CP	5.0		5.0		
$t_H(H)$	Hold Time	0.0		0.0		ns
$t_H(L)$	I/O_n to CP	0.0		0.0		
$t_S(H)$	Setup Time	9.5		10.0		ns
$t_S(L)$	S_n to CP	9.5		10.0		
$t_H(H)$	Hold Time	0.0		0.0		ns
$t_H(L)$	S_n to CP	0.0		0.0		
$t_S(H)$	Setup Time	7.0		7.0		ns
$t_S(L)$	$\overline{CET}$ to CP	7.0		7.0		
$t_H(H)$	Hold Time	0.0		0.0		ns
$t_H(L)$	$\overline{CET}$ to CP	0.0		0.0		
$t_W(H)$	Clock Pulse Width	4.0		4.0		ns
$t_W(L)$	HIGH or LOW	4.0		4.0		

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M16B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

March 1990
Revised August 1999

74F794
8-Bit Register with Readback

General Description

The 74F794 is an 8-bit register with readback capability designed to store data as well as read the register information back onto the data bus. The I/O bus (D bus) has 3-STATE outputs. Current sinking capability is 64 mA on both the D and Q busses.

Data is loaded into the registers on the LOW-to-HIGH transition of the clock (CP). The output enable ($\overline{OE}$) is used to enable data on D_0–D_7. When $\overline{OE}$ is LOW, the output of the registers is enabled on D_0–D_7, enabling D as an output bus. When OE is HIGH, D_0–D_7 are inputs to the registers configuring D as an input bus.

Features

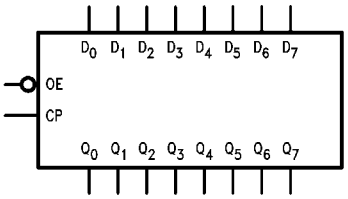
- 3-STATE outputs on the I/O port
- D and Q output sink capability of 64 mA
- Functionally and pin equivalent to the 74LS794

Ordering Code:

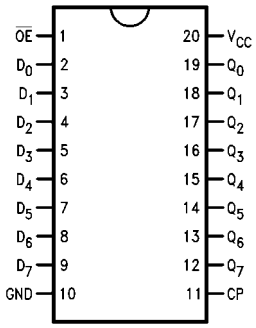
Order Number	Package Number	Package Description
74F794SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F794PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Input Loading/Fan-Out

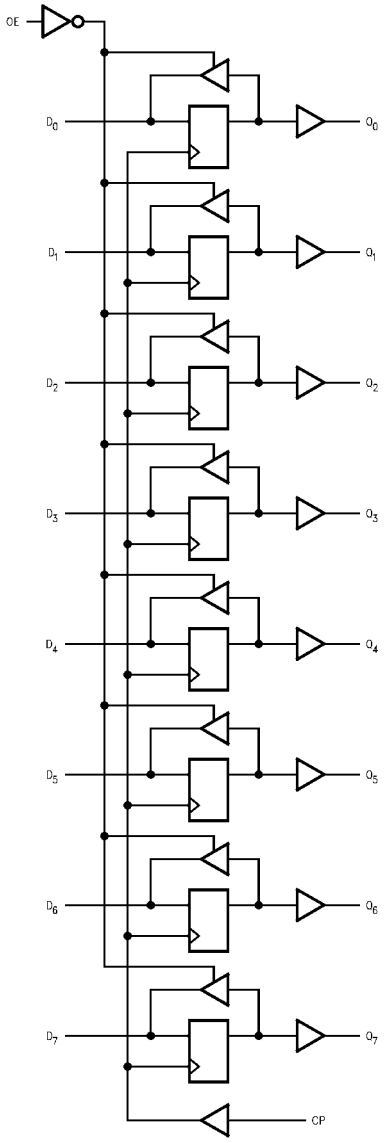
Pin Names	Description	HIGH/LOW	
		(U.L.)	Current
$\overline{OE}$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
CP	Clock Pulse Inputs	1.0/1.0	20 µA/–0.6 mA
D_0–D_7	D Bus Inputs/	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	750/106.6	–15 mA/64 mA
Q_0–Q_7	Q Bus Outputs	750/106.6	–15 mA/64 mA

Truth Table

Inputs		Outputs	
CP	$\overline{OE}$	Q	D
L or H or ↓	L	Q_n	Output, Q
L or H or ↓	H	Q_n	Input
↑	L	Q_n	Output, Q (Note 1)
↑	H	D	Input

Note 1: In this case the output of the register is clocked to the inputs and the overall Q output is unchanged at Q_n.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Storage Temperature	−65°C to + 150°C
Ambient Temperature under Bias	−55° to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
ESD Last Passing Voltage (Min)	4000V
Voltage Applied to Output	
In HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to 70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: In this case the output of the register is clocked to the inputs and the overall Q output is unchanged at Q_n.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

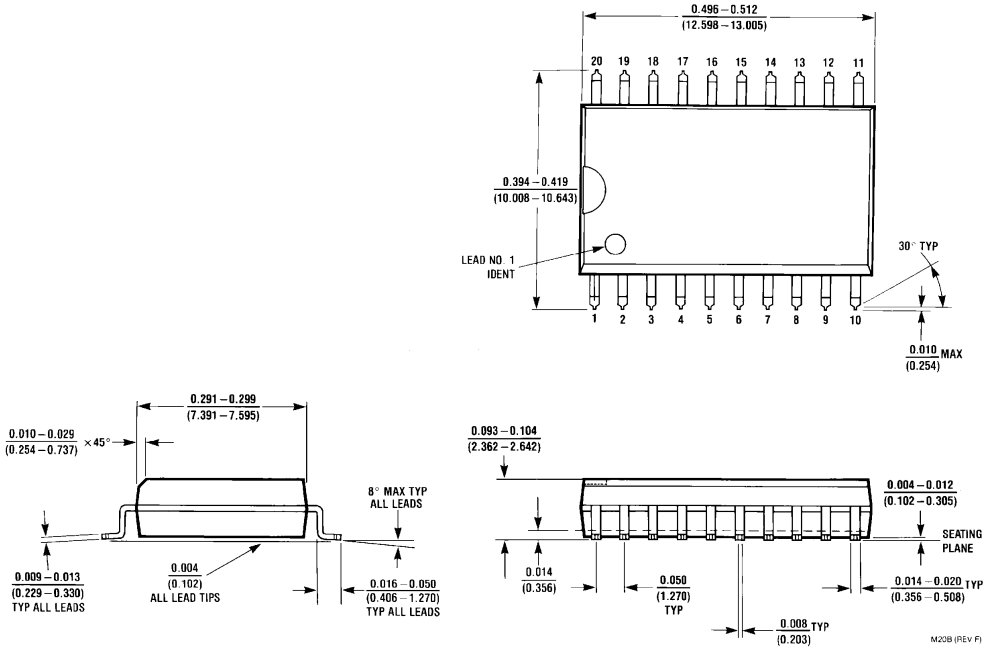
DC Electrical Characteristics over Operating Temperature Range unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4 2.0	2.8 2.44		V	Min	I_{OH} = −3 mA I_{OH} = −15 mA
V_{OL}	Output LOW Voltage		0.45	0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, CP)
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (D_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V ($\overline{OE}$, CP)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{IH} + I_{OZH}	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (Dn)
I_{IL} + I_{OZL}	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (Dn)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			65	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			80	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			80	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

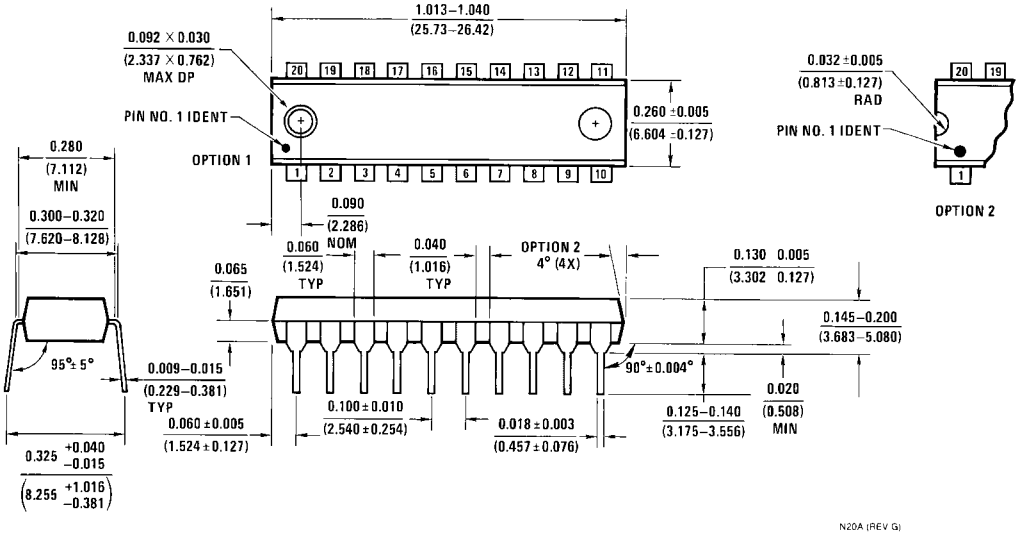
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	90			90		MHz
t_{PLH}	Propagation Delay	2.5		7.0	2.5	8.0	ns
t_{PHL}	CP to Q_n	2.5		8.0	2.5	9.0	
t_{PZH}	Output Enable Time	2.3		8.5	2.0	9.0	ns
t_{PZL}		2.0		10.0	2.0	10.5	
t_{PHZ}	Output Disable Time	1.0		7.0	1.0	8.0	ns
t_{PLZ}		1.0		7.0	1.0	8.0	
$t_S(H)$	Setup Time, HIGH or LOW	4.0			4.0		ns
$t_S(L)$	Bus to Clock	4.0			4.0		
$t_H(H)$	Hold Time, HIGH or LOW	1.5			1.5		ns
$t_H(L)$	Bus to Clock	1.5			1.5		
$t_W(H$	Clock Pulse Width	5.8			5.8		ns
	HIGH or LOW	5.8			5.8		

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F821
10-Bit D-Type Flip-Flop

General Description

The 74F821 is a 10-bit D-type flip-flop with 3-STATE true outputs arranged in a broadside pinout.

Features

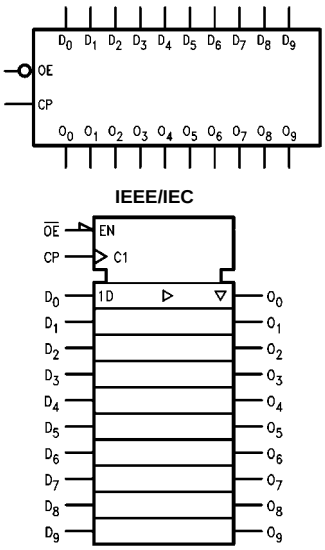
- 3-STATE Outputs

Ordering Code:

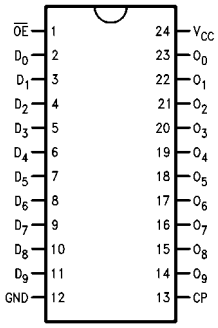
Order Number	Package Number	Package Description
74F821SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F821SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_9	Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	Output Enable 3-STATE Input	1.0/1.0	20 µA/–0.6 mA
CP	Clock Input	1.0/1.0	20 µA/–0.6 mA
O_0–O_9	3-STATE Outputs	150/40 (33.3)	–3.0 mA/24 mA (20 mA)

Functional Description

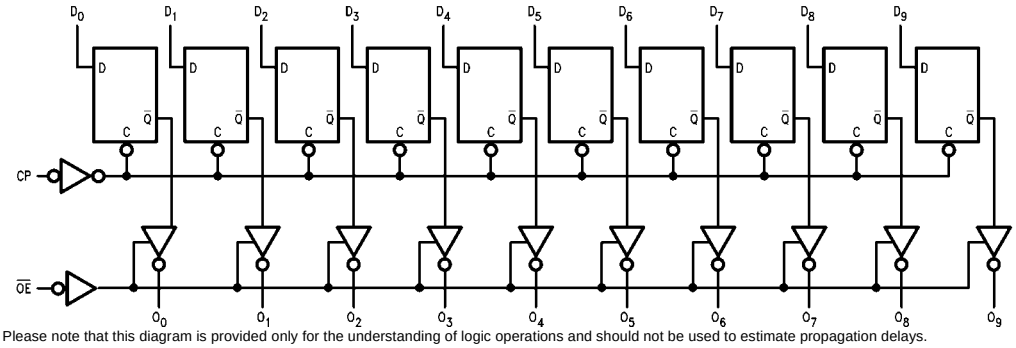
The 74F821 consists of ten D-type edge-triggered flip-flops. This device has 3-STATE true outputs for bus systems organized in a broadside pinning. The buffered Clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH CP transition. With the $\overline{OE}$ LOW the content of the flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Function Table

Inputs			Internal	Output	Function
$\overline{OE}$	CP	D	$\overline{Q}$	O	
H	H	X	NC	Z	Hold
H	L	X	NC	Z	Hold
H	⌐	L	H	Z	Load
H	⌐	H	L	Z	Load
L	⌐	L	H	L	Data Available
L	⌐	H	L	H	Data Available
L	H	X	NC	NC	No Change in Data
L	L	X	NC	NC	No Change in Data

L = LOW Voltage Level
H = HIGH Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCZ}	Power Supply Current			78	100	mA	Max	V_O = HIGH Z

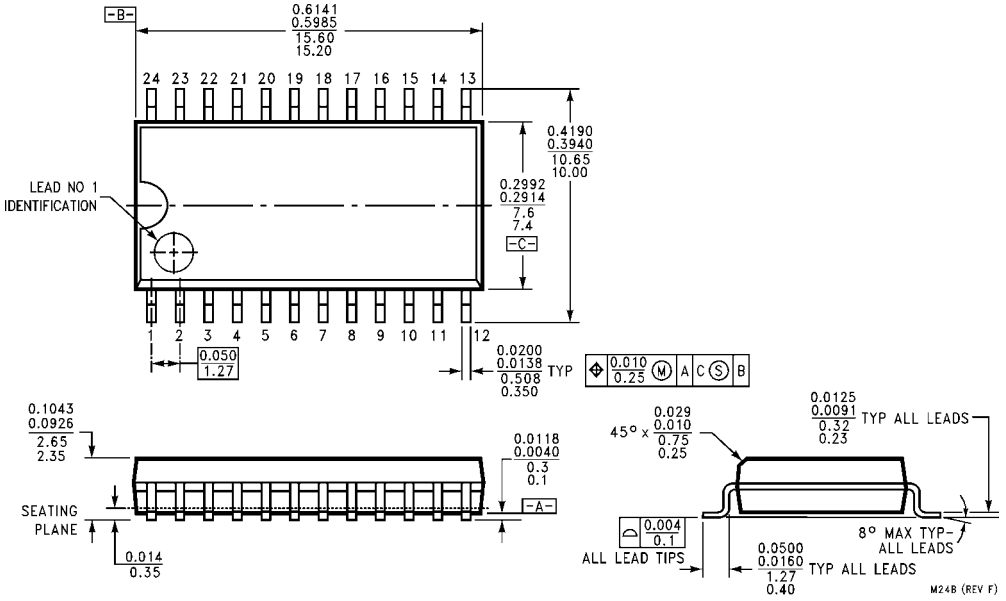
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	150		60		70		MHz
t_{PLH}	Propagation Delay	2.0	6.4	9.5	2.0	10.5	2.0	10.5	ns
t_{PHL}	CP to O_n	2.0	6.2	9.5	2.0	10.5	2.0	10.5	
t_{PZH}	Output Enable Time	2.0	5.8	10.5	2.0	13.0	2.0	11.5	ns
t_{PZL}	$\overline{OE}$ to O_n	2.0	6.3	10.5	2.0	13.0	2.0	11.5	
t_{PHZ}	Output Disable Time	1.5	3.4	7.0	1.0	7.5	1.5	7.5	ns
t_{PLZ}	$\overline{OE}$ to O_n	1.5	3.5	7.0	1.0	7.5	1.5	7.5	

AC Operating Requirements

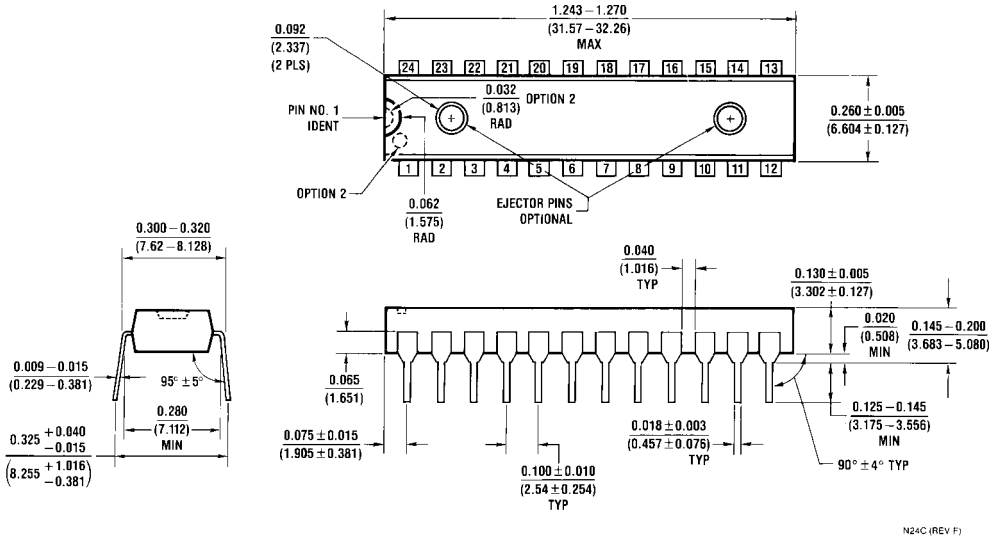
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.5		4.0		3.0		ns
$t_S(L)$	D_n to CP	2.5		4.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.5		2.5		2.5		
$t_H(L)$	D_n to CP	2.5		2.5		2.5		
$t_W(H)$	CP Pulse Width	5.0		6.0		6.0		ns
$t_W(L)$	HIGH or LOW	5.0		6.0		6.0		

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F823
9-Bit D-Type Flip-Flop

General Description

The 74F823 is a 9-bit buffered register. It features Clock Enable and Clear which are ideal for parity bus interfacing in high performance microprogramming systems.

Features

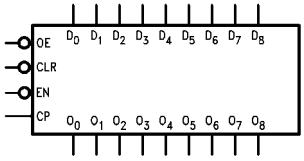
- 3-STATE outputs
- Clock Enable and Clear

Ordering Code:

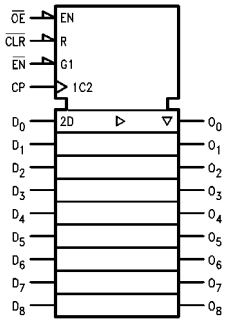
Order Number	Package Number	Package Description
74F823SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F823SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

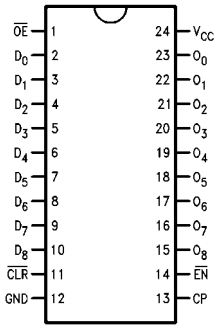
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_8	Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
$\overline{CLR}$	Clear	1.0/1.0	20 µA/–0.6 mA
CP	Clock Input	1.0/2.0	20 µA/–1.2 mA
$\overline{EN}$	Clock Enable	1.0/1.0	20 µA/–0.6 mA
O_0–O_8	3-STATE Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)

Functional Description

The 74F823 device consists of nine D-type edge-triggered flip-flops. It has 3-STATE true outputs and is organized in broadside pinning. The buffered Clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH CP transition. With the $\overline{OE}$ LOW the contents of the flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops. In addition to the Clock and Output Enable pins, the 74F823 has Clear ($\overline{CLR}$) and Clock Enable ($\overline{EN}$) pins.

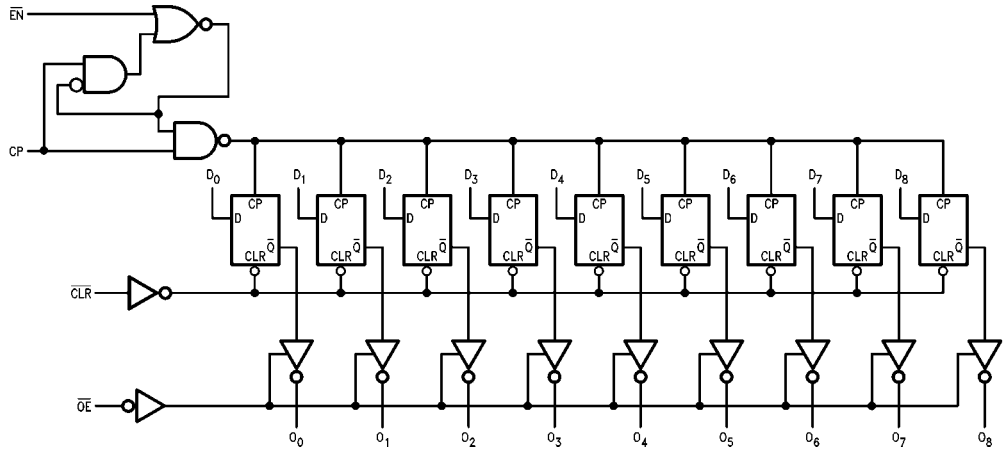
When the $\overline{CLR}$ is LOW and the $\overline{OE}$ is LOW, the outputs are LOW. When $\overline{CLR}$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}$ is HIGH, the outputs do not change state regardless of the data or clock inputs transitions. This device is ideal for parity bus interfacing in high performance systems.

Function Table

Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	D	$\overline{Q}$	O	
H	H	L	H	X	NC	Z	Hold
H	H	L	L	X	NC	Z	Hold
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	L	X	X	X	H	Z	Clear
L	L	X	X	X	H	L	Clear
H	H	L	⌐	H	H	Z	Load
H	H	L	⌐	H	L	Z	Load
L	H	L	⌐	L	H	L	Data Available
L	H	L	⌐	H	L	H	Data Available
L	H	L	H	X	NC	NC	No Change in Data
L	H	L	L	X	NC	NC	No Change in Data

L = LOW Voltage Level
H = HIGH Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V ($\overline{OE}$, $\overline{CLR}$, $\overline{EN}$)
					−1.2	mA	Max	V_{IN} = 0.5V (CP)
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Buss Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			75	100	mA	Max	V_O = HIGH Z

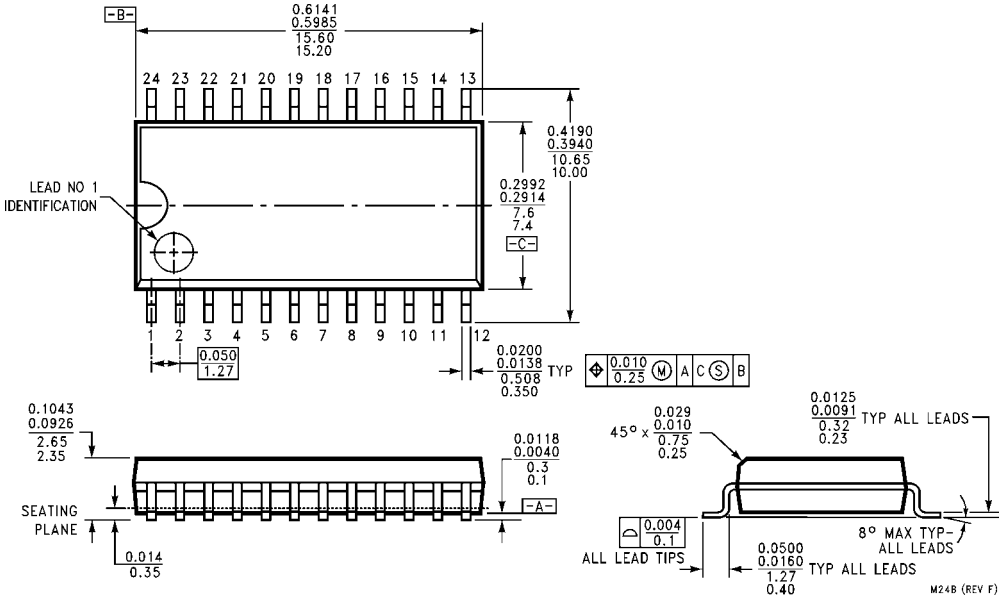
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	160		60		70		MHz
t_{PLH}	Propagation Delay	2.0	5.6	9.5	2.0	10.5	2.0	10.5	ns
t_{PHL}	CP to O_n	2.0	5.2	9.5	2.0	10.5	2.0	10.5	
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	4.0	7.1	12.0	4.0	13.0	4.0	13.0	ns
t_{PZH}	Output Enable Time	2.0	5.8	10.5	2.0	13.0	2.0	11.5	ns
t_{PZL}	$\overline{OE}$ to O_n	2.0	5.5	10.5	2.0	13.0	2.0	11.5	
t_{PHZ}	Output Disable Time	1.5	2.9	7.0	1.0	7.5	1.5	7.5	
t_{PLZ}	$\overline{OE}$ to O_n	1.5	2.7	7.0	1.0	7.5	1.5	7.5	

AC Operating Requirements

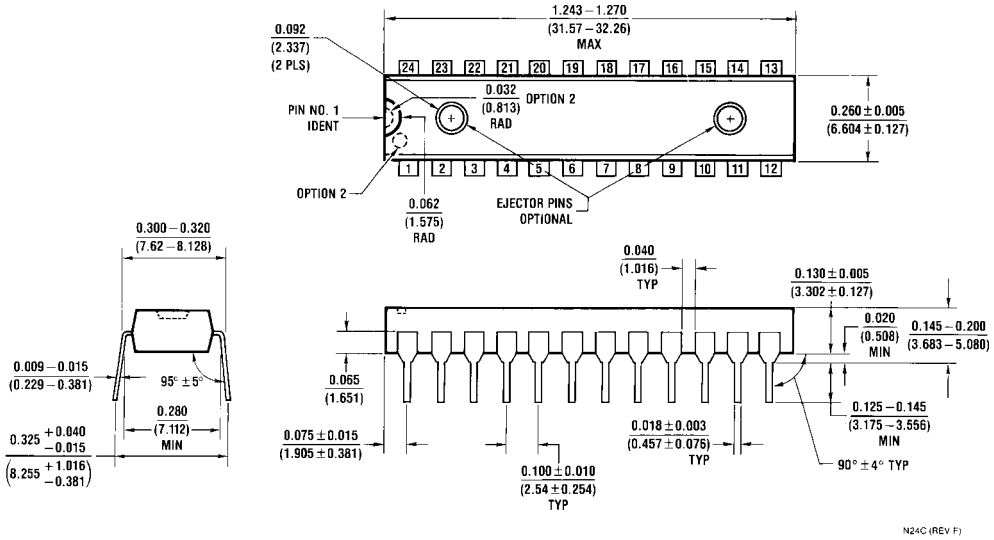
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.5		4.0		3.0		ns
$t_S(L)$	D_n to CP	2.5		4.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.5		2.5		2.5		
$t_H(L)$	D_n to CP	2.5		2.5		2.5		
$t_S(H)$	Setup Time, HIGH or LOW	4.5		5.0		5.0		ns
$t_S(L)$	$\overline{EN}$ to CP	2.5		3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		3.0		2.0		
$t_H(L)$	$\overline{EN}$ to CP	0		1.0		0		
$t_W(H)$	CP Pulse Width	5.0		6.0		6.0		ns
$t_W(L)$	HIGH or LOW	5.0		6.0		6.0		
$t_W(L)$	$\overline{CLR}$ Pulse Width, LOW	5.0		5.0		5.0		ns
t_{REC}	$\overline{CLR}$ Recovery Time	5.0		5.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F825
8-Bit D-Type Flip-Flop

General Description

The 74F825 is an 8-bit buffered register. It has Clock Enable and Clear features which are ideal for parity bus interfacing in high performance microprogramming systems. Also included in the 74F825 are multiple enables that allow multi-user control of the interface.

Features

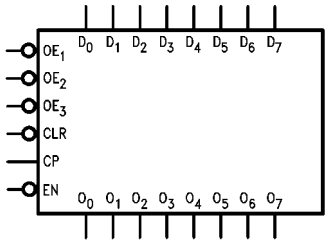
- 3-STATE output
- Clock enable and clear
- Multiple output enables

Ordering Code:

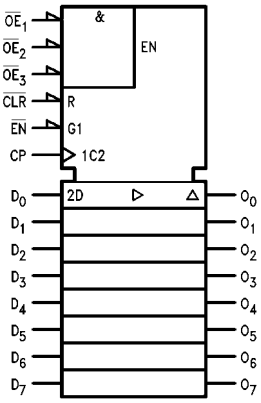
Order Number	Package Number	Package Description
74F825SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F825SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

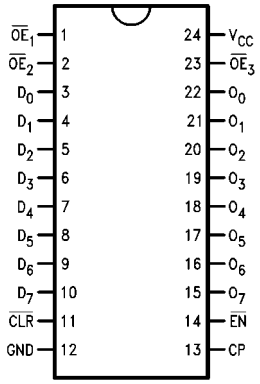
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 µA/–0.6 mA
O_0–O_7	3-STATE Data Outputs	150/40 (33.3)	–3 mA/24 mA (20 mA)
$\overline{OE}_1$, $\overline{OE}_2$, $\overline{OE}_3$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
$\overline{EN}$	Clock Enable	1.0/1.0	20 µA/–0.6 mA
$\overline{CLR}$	Clear	1.0/1.0	20 µA/–0.6 mA
CP	Clock Input	1.0/2.0	20 µA/–1.2 mA

Functional Description

The 74F825 consists of eight D-type edge-triggered flip-flops. This device has 3-STATE true outputs and is organized in broadside pinning. In addition to the clock and output enable pins, the buffered clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH CP transition. With the $\overline{OE}$ LOW the contents of the flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops. The 74F825 has Clear ($\overline{CLR}$) and Clock Enable ($\overline{EN}$) pins.

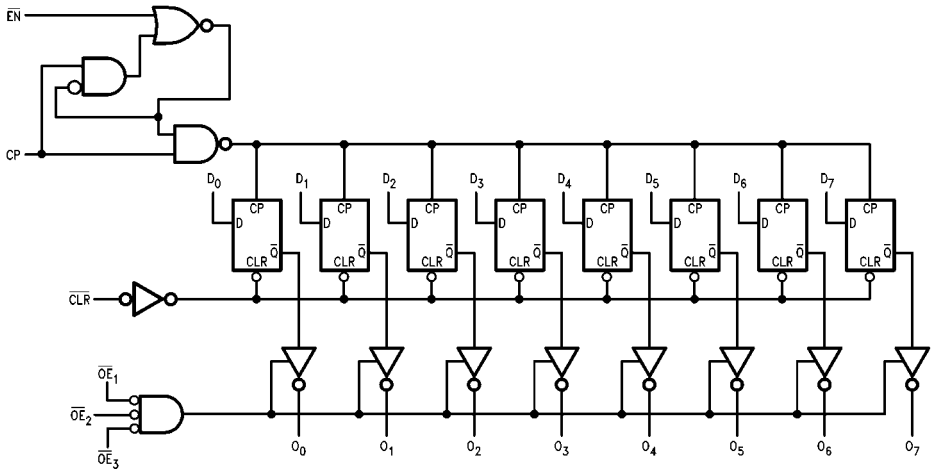
When the $\overline{CLR}$ is LOW and the $\overline{OE}$ is LOW the outputs are LOW. When $\overline{CLR}$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}$ is HIGH the outputs do not change state, regardless of the data or clock input transitions.

Function Table

Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	D	$\overline{Q}$	O	
H	H	L	H	X	NC	Z	Hold
H	H	L	L	X	NC	Z	Hold
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	L	X	X	X	H	Z	Clear
L	L	X	X	X	H	L	Clear
H	H	L	↗	L	H	Z	Load
H	H	L	↗	H	L	Z	Load
L	H	L	↗	L	H	L	Data Available
L	H	L	↗	H	L	H	Data Available
L	H	L	H	X	NC	NC	No Change in Data
L	H	L	L	X	NC	NC	No Change in Data

L = LOW Voltage Level
H = HIGH Voltage Level
X = Immaterial
Z = High Impedance
↗ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Buss Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			75	90	mA	Max	V_O = HIGH Z

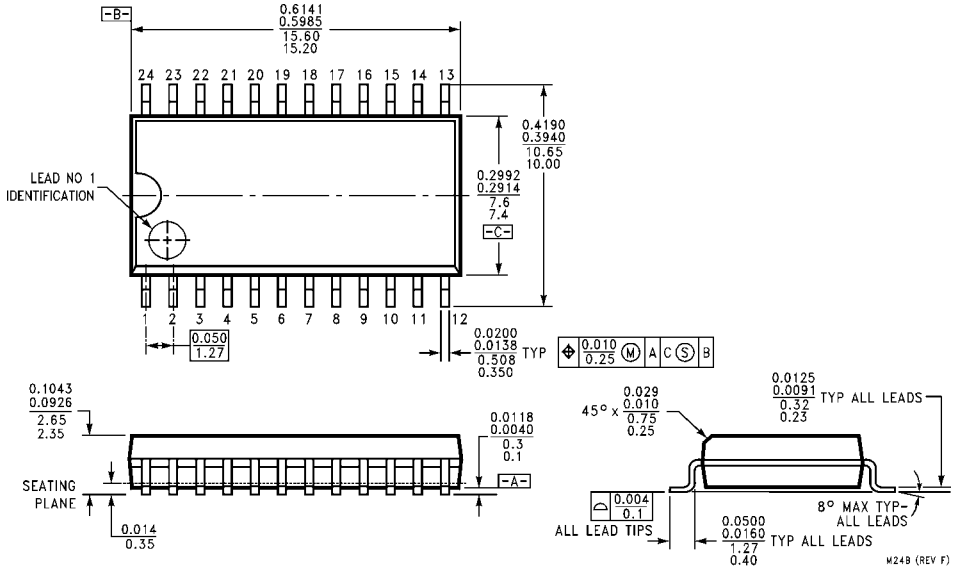
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	100	160		60		70		MHz
t_{PLH}	Propagation Delay	2.0	6.5	9.5	2.0	10.5	2.0	10.5	ns
t_{PHL}	CP to O_n	2.0	6.6	9.5	2.0	10.5	2.0	10.5	
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	4.0	7.4	12.0	4.0	13.0	4.0	13.0	ns
t_{PZH}	Output Enable Time	2.0	6.5	10.5	2.0	13.0	2.0	11.5	ns
t_{PZL}	$\overline{OE}$ to O_n	2.0	6.6	10.5	2.0	13.0	2.0	11.5	
t_{PHZ}	Output Disable TIme	1.5	3.5	7.0	1.0	7.5	1.5	7.5	
t_{PLZ}	$\overline{OE}$ to O_n	1.5	3.3	7.0	1.0	7.5	1.5	7.5	

AC Operating Requirements

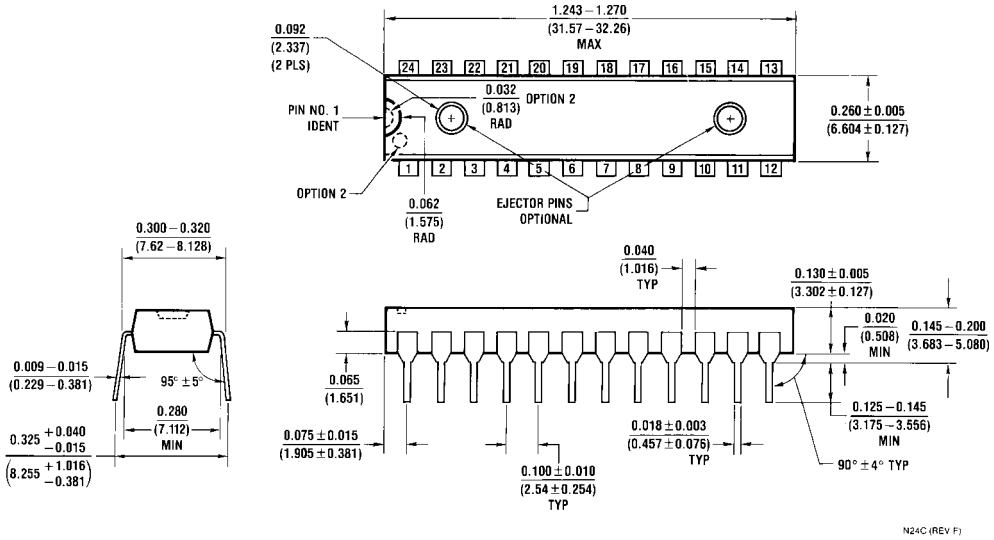
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.5		4.0		3.0		ns
$t_S(L)$	D_n to CP	2.5		4.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.5		2.5		2.5		
$t_H(L)$	D_n to CP	2.5		2.5		2.5		
$t_S(H)$	Setup Time, HIGH or LOW	4.5		5.0		5.0		ns
$t_S(L)$	$\overline{EN}$ to CP	2.5		3.0		3.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		3.0		1.0		
$t_H(L)$	$\overline{EN}$ to CP	0		2.0		0		
$t_W(H)$	CP Pulse Width	5.0		6.0		6.0		ns
$t_W(L)$	HIGH or LOW	5.0		6.0		6.0		
$t_W(L)$	$\overline{CLR}$ Pulse Width, LOW	5.0		5.0		5.0		ns
t_{REC}	$\overline{CLR}$ Recovery Time	5.0		5.0		5.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F827 • 74F828
10-Bit Buffers/Line Drivers

General Description

The 74F827 and 74F828 10-bit bus buffers provide high performance bus interface buffering for wide data/address paths or buses carrying parity. The 10-bit buffers have NOR output enables for maximum control flexibility.

The 74F828 is an inverting version of the 74F827.

Features

- 3-STATE output
- 74F828 is inverting

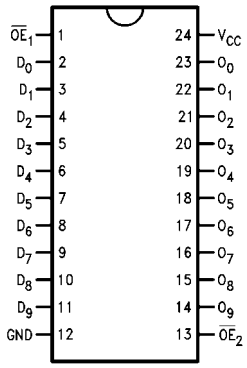
Ordering Code:

Order Number	Package Number	Package Description
74F827SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F827SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
74F828SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F828SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

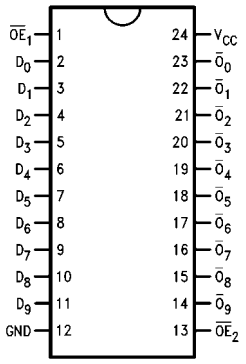
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

74F827

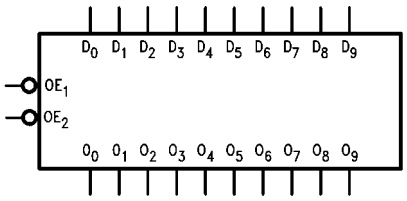


74F828

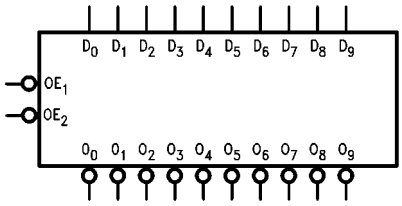


Logic Symbols

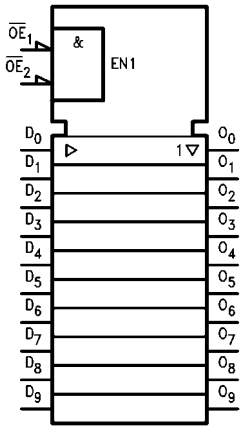
74F827



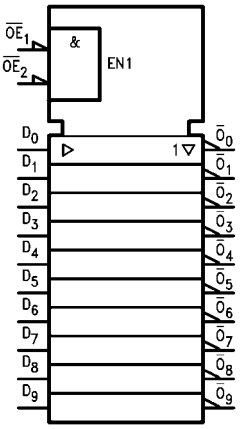
74F828



IEEE/IEC
74F827



IEEE/IEC
74F828



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
D_0–D_7	Data Inputs	1.0/1.0	20 µA/–0.6 mA
O_0–O_7	Data Outputs, 3-STATE	600/106.6 (80)	–12 mA/64 mA (48 mA)

Functional Description

The 74F827 and 74F828 are line drivers designed to be employed as memory address drivers, clock drivers and bus-oriented transmitters/receivers which provide improved PC board density. The devices have 3-STATE outputs controlled by the Output Enable ($\overline{OE}$) pins. The outputs can sink 64 mA and source 15 mA. Input clamp diodes limit high-speed termination effects.

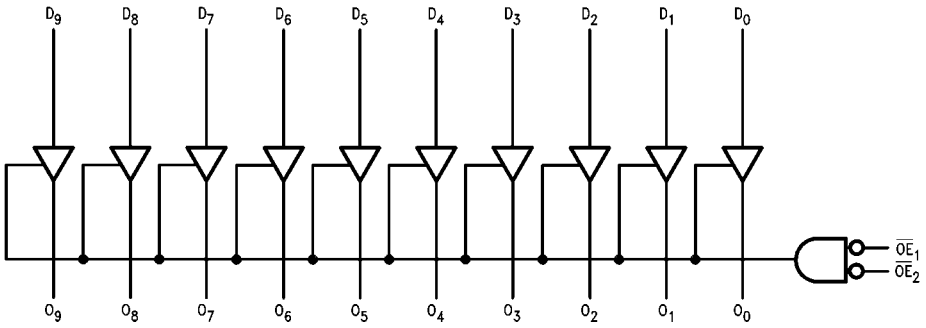
Function Table

Inputs		Outputs		Function
$\overline{OE}$	D_n	O_n		
		74F827	74F828	
L	H	H	L	Transparent
L	L	L	H	Transparent
H	X	Z	Z	High Z

H = HIGH Voltage level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial

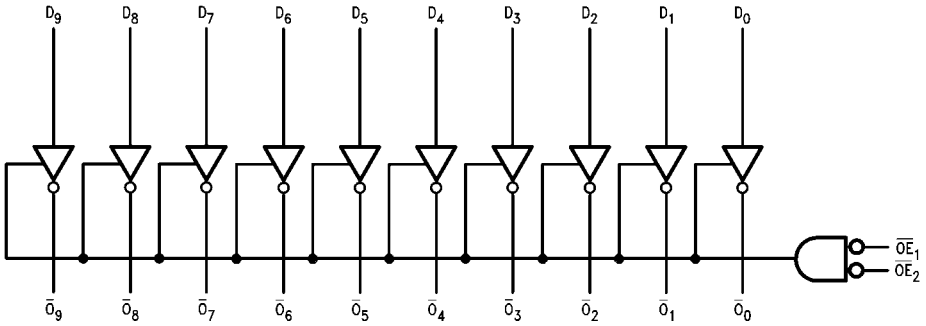
Logic Diagrams

74F827



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

74F828



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

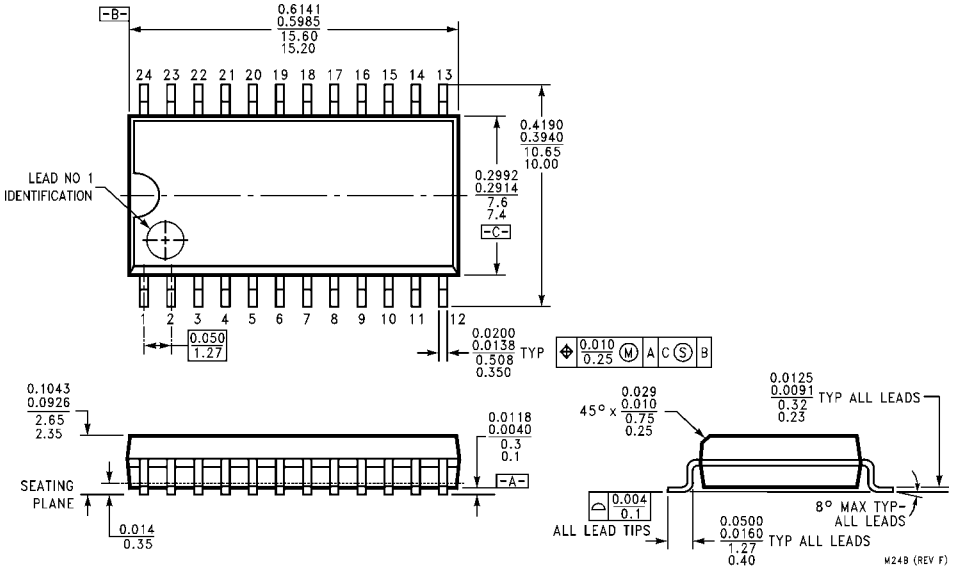
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		10% V_{CC}	2.0					I_{OH} = −15 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current (74F827)			30	45	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F827)			60	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F827)			40	60	mA	Max	V_O = HIGH Z
I_{CCH}	Power Supply Current (74F828)			14	20	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current (74F828)			56	85	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current (74F828)			35	50	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

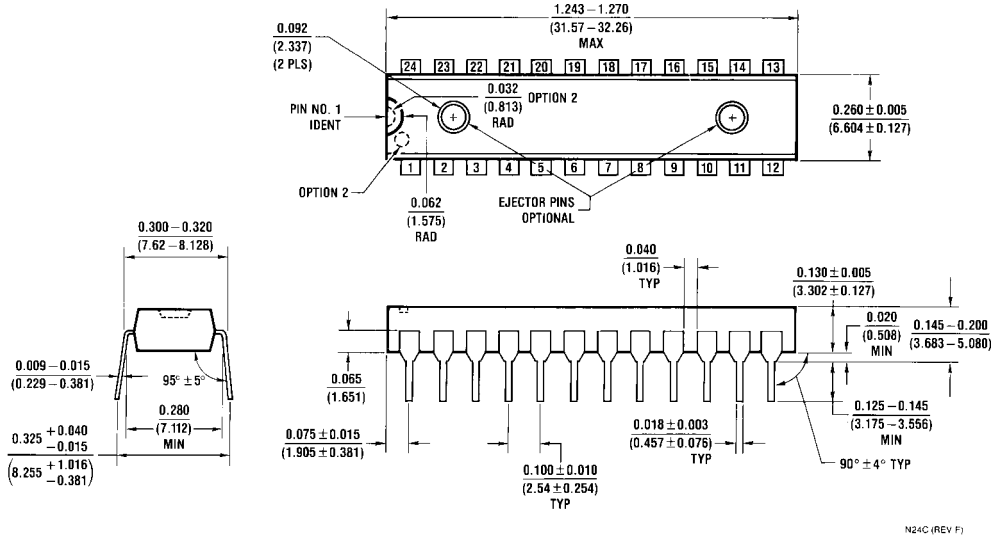
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	3.0	5.5	1.0	7.5	1.0	6.5	ns
t_{PHL}	Data to Output (74F827)	1.5	3.3	5.5	1.5	7.0	1.5	6.0	
t_{PLH}	Propagation Delay	1.0	3.0	5.0			1.0	5.5	ns
t_{PHL}	Data to Output (74F828)	1.0	2.0	4.0			1.0	4.0	
t_{PZH}	Output Enable Time	3.0	5.7	9.0	2.5	10.0	2.5	9.5	ns
t_{PZL}	$\overline{OE}$ to O_n	3.5	6.8	11.5	3.0	12.5	3.0	12.0	
t_{PHZ}	Output Disable Time	1.5	3.3	8.0	1.5	9.0	1.5	8.5	ns
t_{PLZ}	$\overline{OE}$ to O_n	1.0	3.5	8.0	1.0	9.0	1.0	8.5	

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

March 1988
Revised August 1999

74F841
10-Bit Transparent Latch

General Description

The 74F841 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths or buses carrying parity. The 74F841 is a 10-bit transparent latch, a 10-bit version of the 74F373.

Features

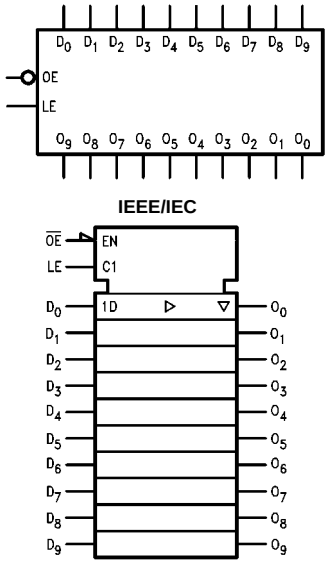
- 3-STATE output

Ordering Code:

Order Number	Package Number	Package Description
74F841SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F841SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

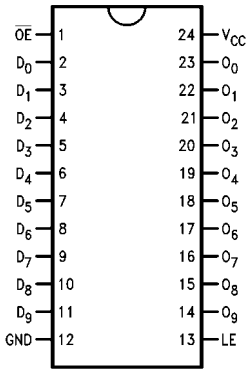
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_9	Data Inputs	1.0/1.0	20 µA/–0.6 mA
O_0–O_9	3-STATE Outputs	150/40	–3 mA/24 mA
$\overline{OE}$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
LE	Latch Enable	1.0/1.0	20 µA/–0.6 mA

Functional Description

The 74F841 device consists of ten D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition.

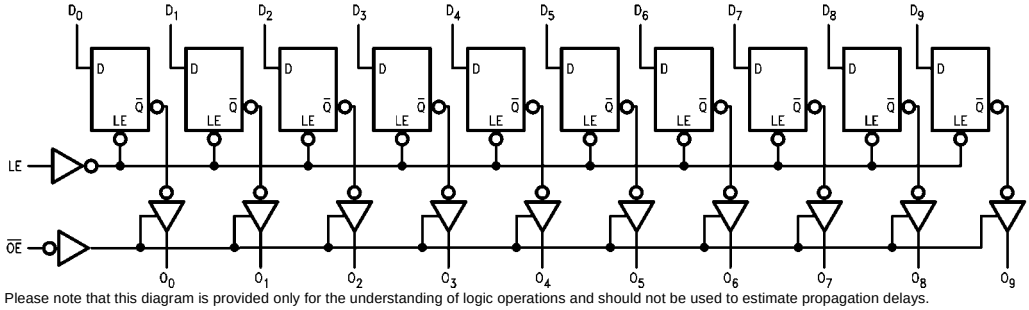
On the LE HIGH-to-LOW transition, the data that meets the setup and hold time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

Function Table

Inputs			Internal	Output	Function
$\overline{OE}$	LE	D	Q	O	
X	X	X	X	Z	High Z
H	H	L	L	Z	High Z
H	H	H	H	Z	High Z
H	L	X	NC	Z	Latched
L	H	L	L	L	Transparent
L	H	H	H	H	Transparent
L	L	X	NC	NC	Latched
L	X	X	H	H	Preset
L	X	X	L	L	Clear
L	X	X	H	H	Preset
H	L	X	L	Z	Latched
H	L	X	H	Z	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			69	92	mA	Max	V_O = HIGH Z

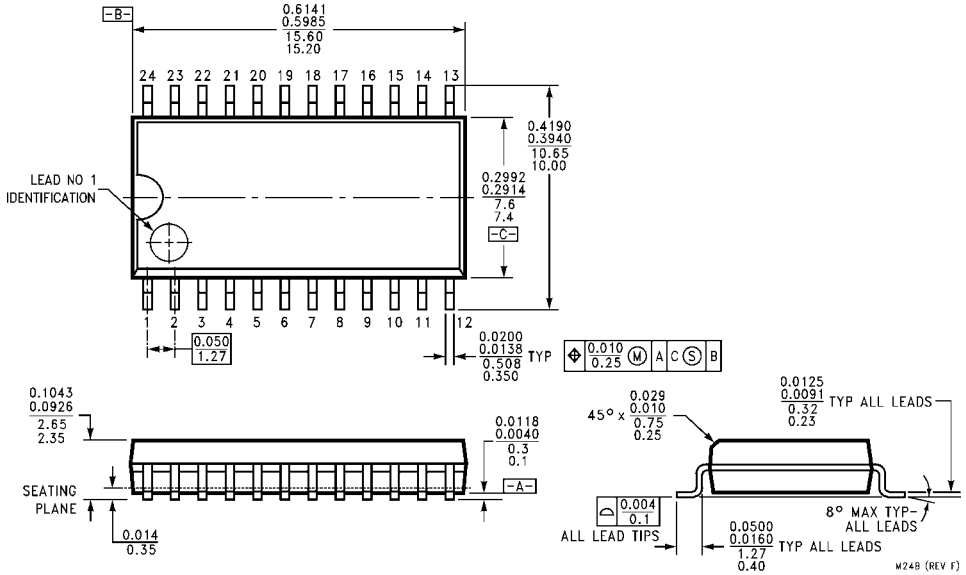
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5		8.0	2.0	9.0	ns
t_{PHL}	D_n to O_n	1.5		6.5	1.5	7.0	
t_{PLH}	Propagation Delay	5.0		12.0	4.5	13.5	ns
t_{PHL}	LE to O_n	2.0		7.5	2.0	8.0	
t_{PZH}	Output Enable Time	2.5		8.5	2.0	9.5	ns
t_{PZL}	$\overline{OE}$ to O_n	2.5		9.0	2.0	10.0	
t_{PHZ}	Output Disable Time	1.0		6.5	1.0	7.5	
t_{PLZ}	$\overline{OE}$ to O_n	1.0		6.5	1.0	7.5	

AC Operating Requirements

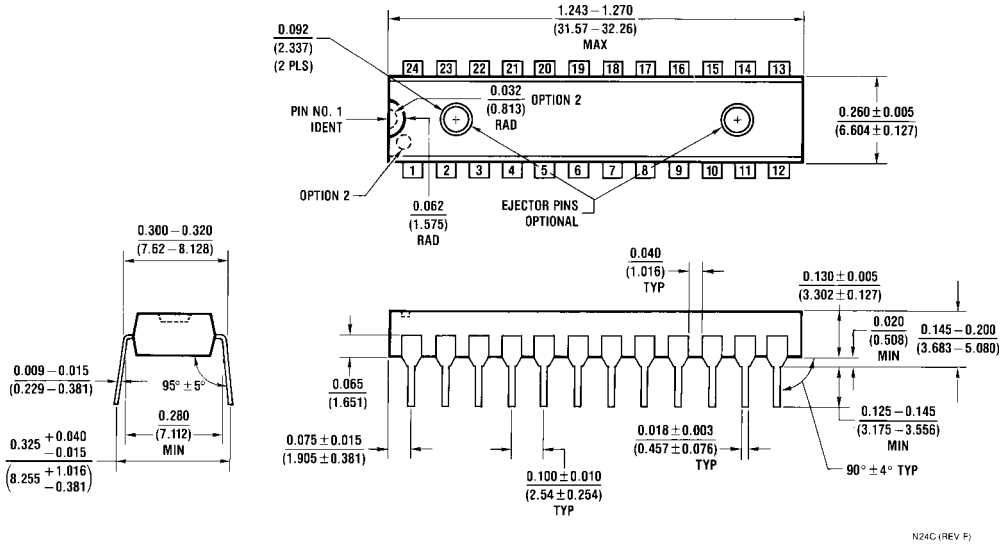
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.5		ns
$t_S(L)$	D_n to LE	2.0		2.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.5		3.0		
$t_H(L)$	D_n to LE	3.0		3.5		
$t_W(H)$	LE Pulse Width, HIGH	4.0		4.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

January 1988
Revised July 1999

74F843
9-Bit Transparent Latch

General Description

The 74F843 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths or buses carrying parity.

Features

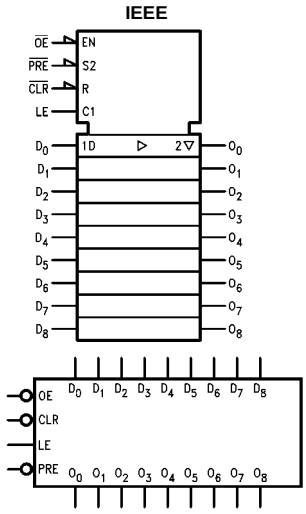
- 3-STATE output

Ordering Code:

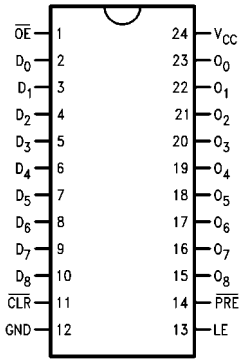
Order Number	Package Number	Package Description
74F843SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F843SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_8	Data Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{OE}$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
LE	Latch Enable	1.0/1.0	20 µA/–0.6 mA
$\overline{CLR}$	Clear	1.0/1.0	20 µA/–0.6 mA
$\overline{PRE}$	Preset	1.0/1.0	20 µA/–0.6 mA
O_0–O_8	3-STATE Data Outputs	150/40	–3 mA/24 mA

Functional Description

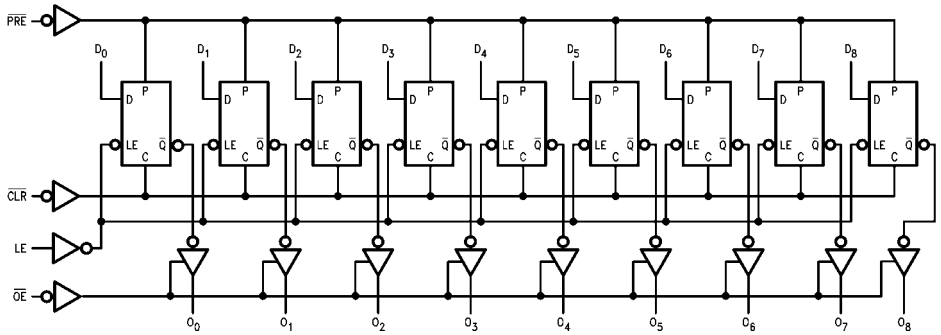
The 74F843 consists of nine D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition. On the LE HIGH-to-LOW transition, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state. In addition to the LE and $\overline{OE}$ pins, the 74F843 has a Clear ($\overline{CLR}$) pin and a Preset ($\overline{PRE}$). These pins are ideal for parity bus interfacing in high performance systems. When $\overline{CLR}$ is LOW, the outputs are LOW if $\overline{OE}$ is LOW. When $\overline{CLR}$ is HIGH, data can be entered into the latch. When $\overline{PRE}$ is LOW, the Outputs are HIGH if $\overline{OE}$ is LOW. Preset overrides $\overline{CLR}$.

Function Table

Inputs					Internal	Output	Function
$\overline{CLR}$	$\overline{PRE}$	$\overline{OE}$	LE	D	Q	O	
H	H	X	X	X	X	Z	High Z
H	H	H	H	L	L	Z	High Z
H	H	H	H	H	H	Z	High Z
H	H	H	L	X	NC	Z	Latched
H	H	L	H	L	L	L	Transparent
H	H	L	H	H	H	H	Transparent
H	H	L	L	X	NC	NC	Latched
H	L	L	X	X	H	H	Preset
L	H	L	X	X	L	L	Clear
L	L	L	X	X	H	H	Preset
L	H	H	L	X	L	Z	Latched
H	L	H	L	X	H	Z	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	10% V_{CC}	2.5					I_{OH} = −1 mA
	Voltage	10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CC}	Power Supply Current			65	90	mA	Max	

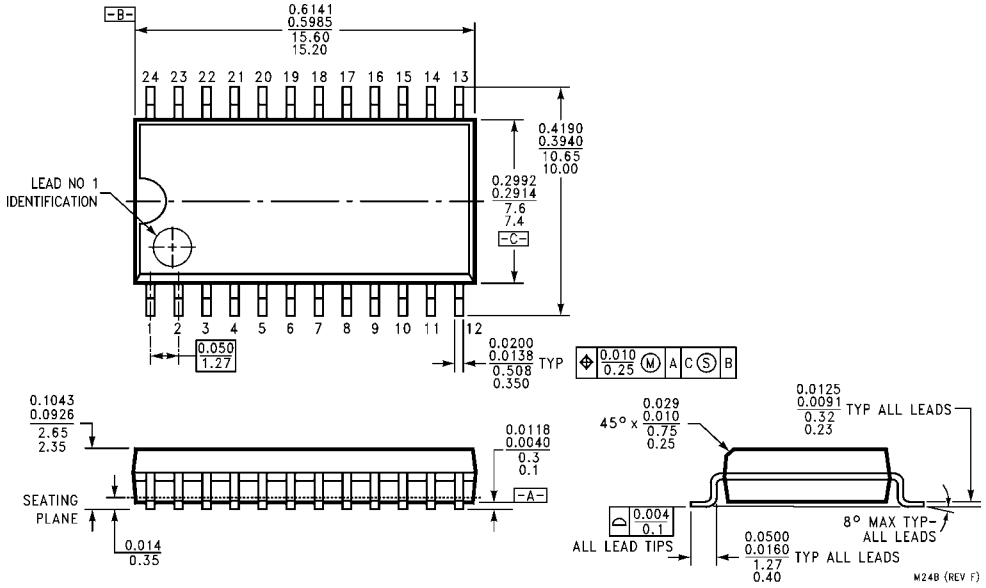
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	5.4	8.0	2.0	9.0	ns
t_{PHL}	D_n to O_n	1.5	4.2	6.5	1.5	7.0	
t_{PLH}	Propagation Delay	5.0	8.5	12.0	4.5	13.5	ns
t_{PHL}	LE to O_n	2.0	4.7	7.5	2.0	8.0	
t_{PLH}	Propagation Delay $\overline{PRE}$ to O_n	3.0	7.3	10.0	2.5	11.0	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	3.0	6.9	10.0	2.5	11.0	ns
t_{PZH}	Output Enable Time	2.5	5.0	8.5	2.0	9.5	ns
t_{PZL}	$\overline{OE}$ to O_n	2.5	6.1	9.0	2.0	10.0	
t_{PHZ}	Output Disable Time	1.0	3.6	6.5	1.0	7.5	ns
t_{PLZ}	$\overline{OE}$ to O_n	1.0	3.4	6.5	1.0	7.5	

AC Operating Requirements

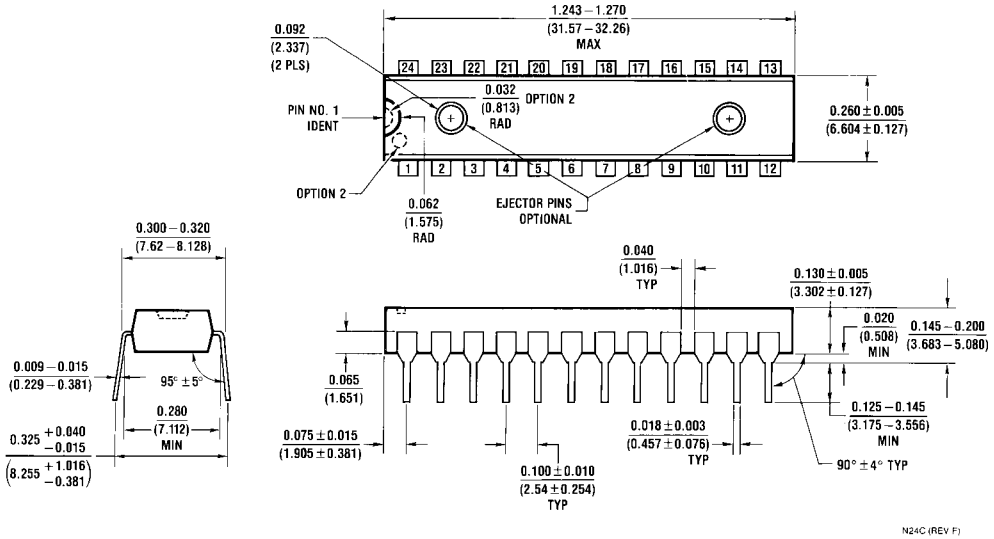
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.5		ns
$t_S(L)$	D_n to LE	2.0		2.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.5		3.0		
$t_H(L)$	D_n to LE	3.0		3.5		
$t_W(H)$	LE Pulse Width, HIGH	4.0		4.0		ns
$t_W(L)$	$\overline{PRE}$ Pulse Width, LOW	5.0		5.0		ns
$t_W(L)$	$\overline{CLR}$ Pulse Width, LOW	5.0		5.0		ns
t_{REC}	$\overline{PRE}$ Recovery Time	10.0		10.0		ns
t_{REC}	$\overline{CLR}$ Recovery Time	12.0		13.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised August 1999

74F845
8-Bit Transparent Latch

General Description

The 74F845 bus interface latch is designed to eliminate the extra packages required to buffer existing latches and provide extra data width for wider address/data paths or buses carrying parity.

The 74F845 is functionally- and pin-compatible with AMD's Am29845.

Features

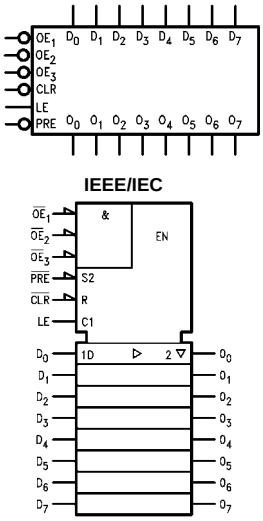
- 3-STATE outputs
- Direct replacement for AMD's Am29845

Ordering Code:

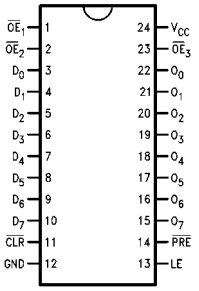
Order Number	Package Number	Package Description
74F845SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F845SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0–D_7	Data Inputs	1.0/1.0	20 µA/–0.6 mA
O_0–O_7	Data Outputs	150/40	–3.0 µA/24 mA
$\overline{OE}_1$–$\overline{OE}_3$	Output Enables	1.0/1.0	20 µA/–0.6 mA
LE	Latch Enable	1.0/1.0	20 µA/–0.6 mA
$\overline{CLR}$	Clear	1.0/1.0	20 µA/–0.6 mA
$\overline{PRE}$	Preset	1.0/1.0	20 µA/–0.6 mA

Functional Description

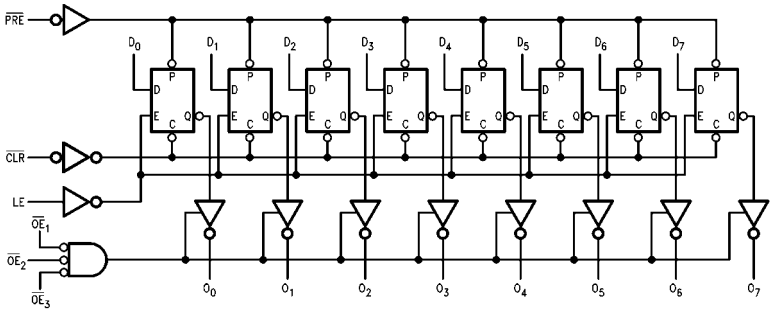
The 74F845 consists of eight D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation as the output transition follows the data in transition. On the LE HIGH-to-LOW transition, the data that meets the setup times is latched. Data appears on the bus when the output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state.

Function Table

Inputs					Internal	Output	Function
$\overline{CLR}$	$\overline{PRE}$	$\overline{OE}$	LE	D	Q	O	
H	H	H	X	X	X	Z	High Z
H	H	H	H	L	L	Z	High Z
H	H	H	H	H	H	Z	High Z
H	H	H	L	X	NC	Z	Latched
H	H	L	H	L	L	L	Transparent
H	H	L	H	H	H	H	Transparent
H	H	L	L	X	NC	NC	Latched
H	L	L	X	X	H	H	Preset
L	H	L	X	X	L	L	Clear
L	L	L	X	X	H	H	Preset
L	H	H	L	X	L	Z	Latched
H	L	H	L	X	H	Z	Latched

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	µA	0.0V	V_{OUT} = 5.25V
I_{CCZ}	Power Supply Current			63	85	mA	Max	V_O = HIGH Z

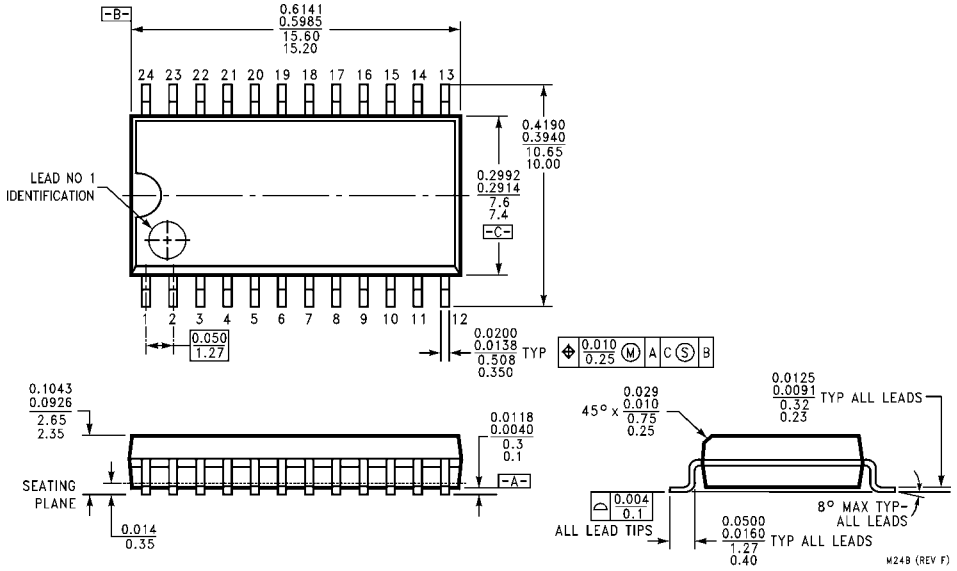
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.8	8.0	2.0	9.0	ns
t_{PHL}	D_n to O_n	1.5	3.6	6.5	1.5	7.0	
t_{PLH}	Propagation Delay	5.0	8.1	12.0	4.5	13.5	ns
t_{PHL}	LE to O_n	2.0	4.4	7.5	2.0	8.0	
t_{PLH}	Propagation Delay $\overline{PRE}$ to O_n	3.0	5.9	10.0	2.5	11.0	ns
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	3.0	6.5	10.0	2.5	11.0	ns
t_{PZH}	Output Enable Time	2.5	5.8	9.5	2.0	10.5	ns
t_{PZL}	$\overline{OE}$ to O_n	2.5	7.6	12.0	2.0	13.0	
t_{PHZ}	Output Disable Time	1.0	3.1	7.5	1.0	8.5	ns
t_{PLZ}	$\overline{OE}$ to O_n	1.0	2.8	6.5	1.0	7.5	

AC Operating Requirements

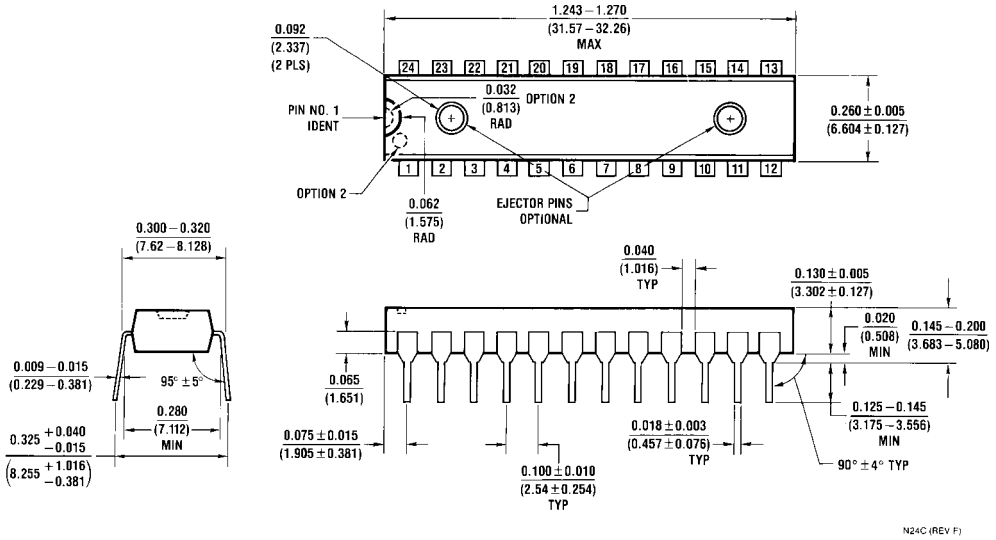
Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.0		2.5		ns
$t_S(L)$	D_n to LE	2.0		2.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.5		3.0		ns
$t_H(L)$	D_n to LE	3.0		3.5		
$t_W(H)$	LE Pulse Width, HIGH	4.0		4.0		ns
$t_W(L)$	$\overline{PRE}$ Pulse Width, LOW	5.0		5.0		ns
$t_W(L)$	$\overline{CLR}$ Pulse Width, LOW	5.0		5.0		ns
t_{REC}	$\overline{PRE}$ Recovery Time	10.0		10.0		ns
t_{REC}	$\overline{CLR}$ Recovery Time	12.0		13.0		ns

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1988
Revised July 1999

74F86
2-Input Exclusive-OR Gate

General Description

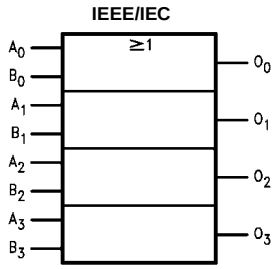
This device contains four independent gates, each of which performs the logic exclusive-OR function.

Ordering Code:

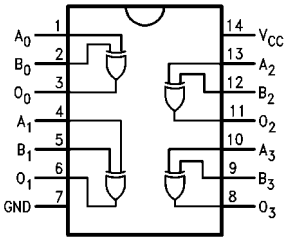
Order Number	Package Number	Package Description
74F86SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F86SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F86PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_n, B_n	Inputs	1.0/1.0	20 μA/–0.6 mA
O_n	Outputs	50/33.3	–1 mA/20 mA

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

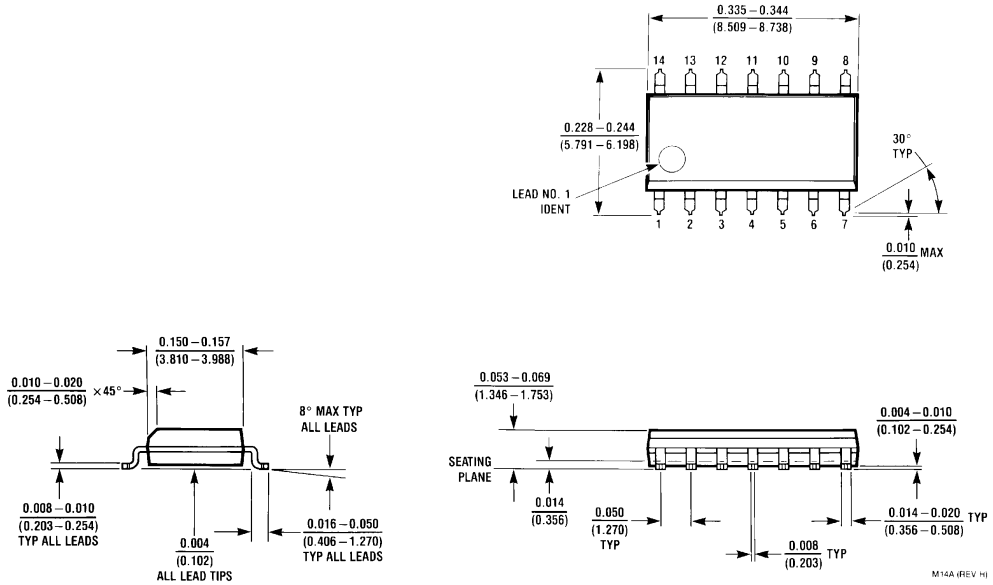
DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −1 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5		Min	I_{OL} = 20 mA
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All other pins grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All other pins grounded
I_{IL}	Input LOW Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{CCH}	Power Supply Current			12	18	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			18	28	mA	Max	V_O = LOW

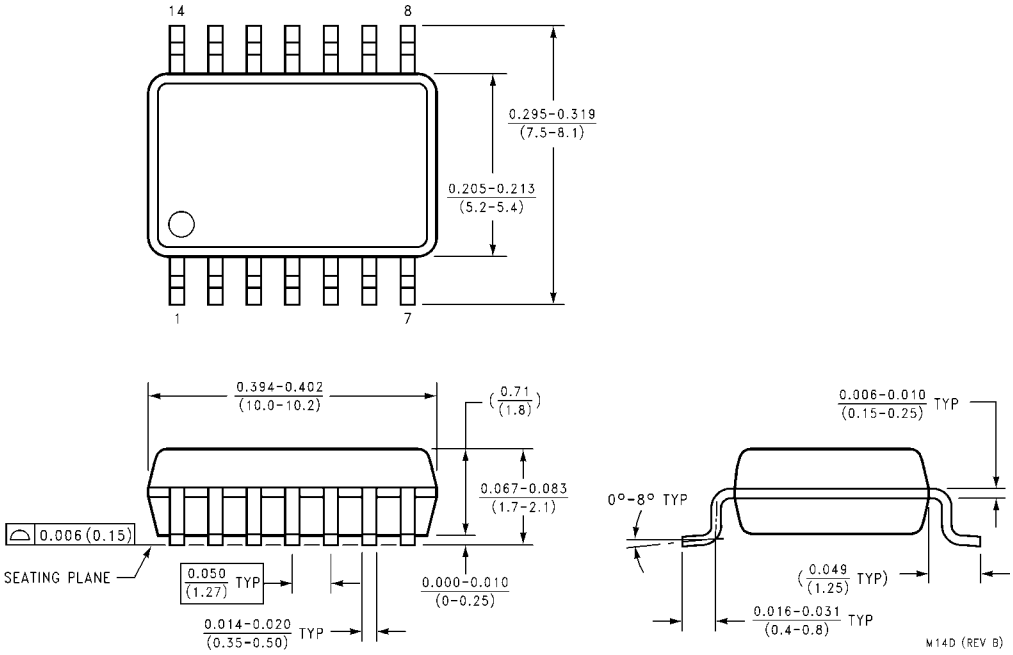
AC Electrical Characteristics

Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to O_n (Other Input LOW)	3.0 3.0	4.0 4.2	5.5 5.5	3.0 3.0	6.5 6.5	ns
t_{PLH} t_{PHL}	Propagation Delay A_n, B_n to O_n (Other Input HIGH)	3.5 3.0	5.3 4.7	7.0 6.5	3.5 3.0	8.0 7.5	ns

Physical Dimensions inches (millimeters) unless otherwise noted

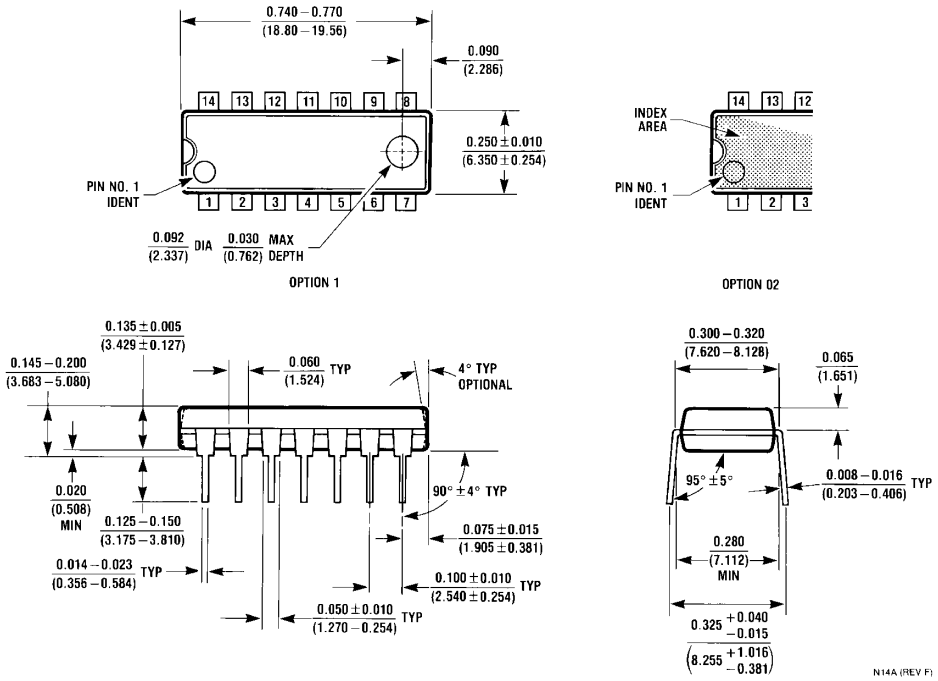


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

February 1989
Revised August 1999

74F899
9-Bit Latchable Transceiver with Parity Generator/Checker

General Description

The 74F899 is a 9-bit to 9-bit parity transceiver with transparent latches. The device can operate as a feed-through transceiver or it can generate/check parity from the 8-bit data busses in either direction. It has a guaranteed current sinking capability of 24 mA at the A-bus and 64 mA at the B-bus.

The 74F899 features independent latch enables for the A-to-B direction and the B-to-A direction, a select pin for ODD/$\overline{\text{EVEN}}$ parity, and separate error signal output pins for checking parity.

Features

- Latchable transceiver with output sink of 24 mA at the A-bus and 64 mA at the B-bus
- Option to select generate parity and check or "feed-through" data/parity in directions A-to-B or B-to-A
- Independent latch enables for A-to-B and B-to-A directions
- Select pin for ODD/$\overline{\text{EVEN}}$ parity
- $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ output pins for parity checking
- Ability to simultaneously generate and check parity
- May be used in systems applications in place of the 74F543 and 74F280
- May be used in system applications in place of the 74F657 and 74F373 (no need to change T/$\overline{\text{R}}$ to check parity)

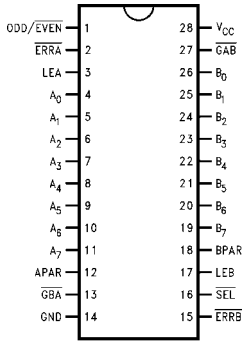
Ordering Code:

Order Number	Package Number	Package Description
74F899SC	M28B	28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74F899QC	V28A	28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square

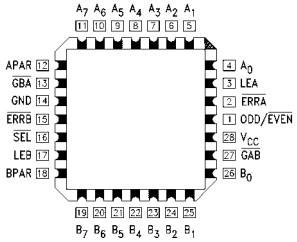
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

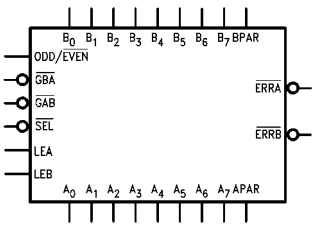
Pin Assignment for SOIC



Pin Assignment for PCC



Logic Symbol



Input Loading/Fan-Out

Pin Names	Description	HIGH/LOW	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Data Inputs/	1.0/1.0	20 µA/–0.6 mA
	Data Outputs	150/40	–3 mA/24 mA
B_0–B_7	Data Inputs/	1.0/1.0	20 µA/–0.6 mA
	Data Outputs	600/106.6	–12 mA/64 mA
APAR	A Bus Parity	1.0/1.0	20 µA/–0.6 mA
	Input/Output	150/40	–3 mA/24 mA
BPAR	B Bus Parity	1.0/1.0	20 µA/–0.6 mA
	Input/Output	600/106.6	–12 mA/64 mA
ODD/$\overline{\text{EVEN}}$	Parity Select Input	1.0/1.0	20 µA/–0.6 mA
$\overline{\text{GBA}}$, $\overline{\text{GAB}}$	Output Enable Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{\text{SEL}}$	Mode Select Input	1.0/1.0	20 µA/–0.6 mA
LEA, LEB	Latch Enable Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{\text{ERRA}}$, $\overline{\text{ERRB}}$	Error Signal Outputs	50/33.3	–1 mA/20 mA

Pin Descriptions

Pin Names	Description
A_0–A_7	A Bus Data Inputs/Data Outputs
B_0–B_7	B Bus Data Inputs/Data Outputs
APAR, BPAR	A and B Bus Parity Inputs
ODD/$\overline{\text{EVEN}}$	ODD/$\overline{\text{EVEN}}$ Parity Select, Active LOW for EVEN Parity
$\overline{\text{GBA}}$, $\overline{\text{GAB}}$	Output Enables for A or B Bus, Active LOW
$\overline{\text{SEL}}$	Select Pin for Feed-Through or Generate Mode, LOW for Generate Mode
LEA, LEB	Latch Enables for A and B Latches, HIGH for Transparent Mode
$\overline{\text{ERRA}}$, $\overline{\text{ERRB}}$	Error Signals for Checking Generated Parity with Parity In, LOW if Error Occurs

Functional Description

The 74F899 has three principal modes of operation which are outlined below. These modes apply to both the A-to-B and B-to-A directions.

- Bus A (B) communicates to Bus B (A), parity is generated and passed on to the B (A) Bus as BPAR (APAR). If LEB (LEA) is HIGH and the Mode Select ($\overline{\text{SEL}}$) is LOW, the parity generated from B[0:7] (A[0:7]) can be checked and monitored by $\overline{\text{ERRB}}$ ($\overline{\text{ERRA}}$).
- Bus A (B) communicates to Bus B (A) in a feed-through mode if $\overline{\text{SEL}}$ is HIGH. Parity is still generated and checked as $\overline{\text{ERRA}}$ and $\overline{\text{ERRB}}$ in the feed-through mode (can be used as an interrupt to signal a data/parity bit error to the CPU).
- Independent Latch Enables (LEA and LEB) allow other permutations of generating/checking (see Function Table).

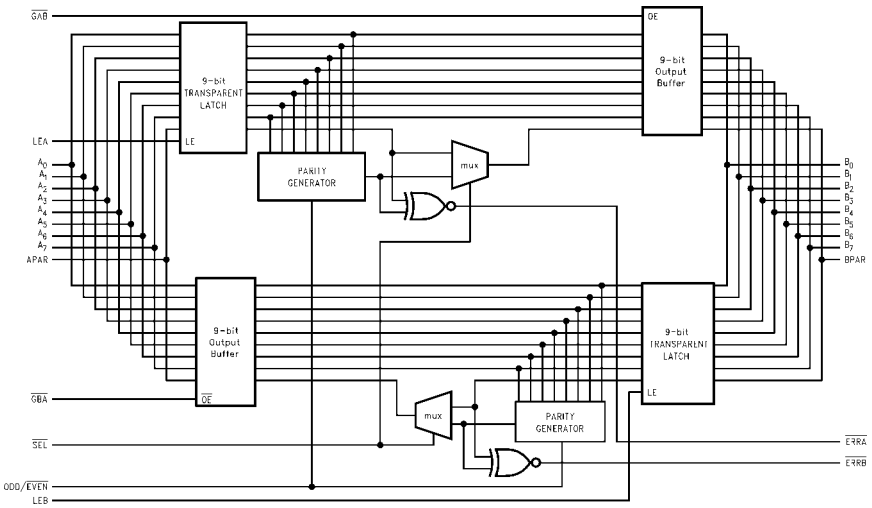
Function Table

Inputs					Operation
$\overline{GAB}$	$\overline{GBA}$	$\overline{SEL}$	LEA	LEB	
H	H	X	X	X	Busses A and B are 3-STATE.
H	L	L	L	H	Generates parity from B[0:7] based on O/$\overline{E}$ (Note 1). Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{ERRB}$.
H	L	L	H	H	Generates parity from B[0:7] based on O/$\overline{E}$. Generated parity → APAR. Generated parity checked against BPAR and output as $\overline{ERRB}$. Generated parity also fed back through the A latch for generate/check as $\overline{ERRA}$.
H	L	L	X	L	Generates parity from B latch data based on O/$\overline{E}$. Generated parity → APAR. Generated parity checked against latched BPAR and output as $\overline{ERRB}$.
H	L	H	X	H	BPAR/B[0:7] → APAR/A0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{ERRB}$.
H	L	H	H	H	BPAR/B[0:7] → APAR/A[0:7] Feed-through mode. Generated parity checked against BPAR and output as $\overline{ERRB}$. Generated parity also fed back through the A latch for generate/check as $\overline{ERRA}$.
L	H	L	H	L	Generates parity for A[0:7] based on O/$\overline{E}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{ERRA}$.
L	H	L	H	H	Generates parity from A[0:7] based on O/$\overline{E}$. Generated parity → BPAR. Generated parity checked against APAR and output as $\overline{ERRA}$. Generated parity also fed back through the B latch for generate/check as $\overline{ERRB}$.
L	H	L	L	X	Generates parity from A latch data based on O/$\overline{E}$. Generated parity → BPAR. Generated parity checked against latched APAR and output as $\overline{ERRA}$.
L	H	H	H	L	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{ERRA}$.
L	H	H	H	H	APAR/A[0:7] → BPAR/B[0:7] Feed-through mode. Generated parity checked against APAR and output as $\overline{ERRA}$. Generated parity also fed back through the B latch for generate/check as $\overline{ERRB}$.

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Note 1: O/$\overline{E}$ = ODD/$\overline{EVEN}$

Functional Block Diagram



Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	10% V_{CC}	2.5			V		I_{OH} = −1 mA
		10% V_{CC}	2.4					I_{OH} = −3 mA
		10% V_{CC}	2.0					I_{OH} = −15 mA (B_n, BPAR)
		5% V_{CC}	2.7					I_{OH} = −1 mA
		5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	10% V_{CC}			0.5	V		I_{OL} = 20 mA (A_n, APAR, $\overline{ERRA}$, $\overline{ERRB}$)
		5% V_{CC}			0.55			I_{OL} = 24 mA (A_n, APAR, $\overline{ERRA}$, $\overline{ERRB}$)
		10% V_{CC}			0.55			I_{OL} = 64 mA (B_n, BPAR)
V_{TH}	Input Threshold Voltage			1.45		V		±0.1V, Sweep Edge Rate must be > 1V/50 ns
V_{OLV}	Negative Ground Bounce Voltage			1.0		V		Observed on “quiet” output during simultaneous switching of remaining outputs
V_{OLP}	Positive Ground Bounce Voltage			1.0		V		Observed on “quiet” output during simultaneous switching of remaining outputs
I_{IL}	Input Low Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{IH}	Input HIGH Current				5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				7.0	µA	Max	V_{IN} = 7.0V (ODD/$\overline{EVEN}$, $\overline{GBA}$, $\overline{GAB}$, $\overline{SEL}$, LEA, LEB)
I_{BVIT}	Input HIGH Current Breakdown (I/O)				0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n, A_{PAR}, B_{PAR})
I_{CEX}	Output HIGH Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current				3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input Low Current				−0.6	mA	Max	V_{IN} = 0.5V
I_{IH+} I_{OZH}	Output Leakage Current				70	µA	Max	$V_{I/O}$ = 2.7V (A_n, B_n, APAR, BPAR)

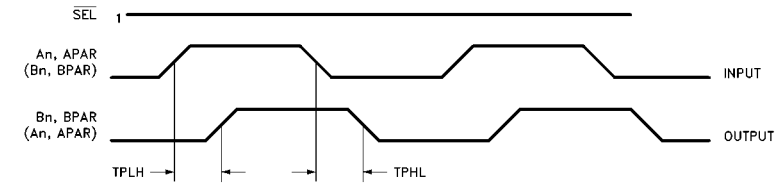
DC Electrical Characteristics (Continued)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
I_{IL+}	Output Leakage			–650	µA	Max	$V_{I/O}$ = 0.5V
I_{OZL}	Current						(A_n, B_n, APAR, BPAR)
I_{OS}	Output Short-Circuit Current	–60		–150	mA	Max	V_{OUT} = 0V
							(A_n, APAR, $\overline{ERRA}$, $\overline{ERRB}$)
		–100		–225		Max	V_{OUT} = 0V (B_n, BPAR)
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		132	155	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		178	210	mA	Max	V_O = LOW, GAB = LOW,
							GBA = HIGH, V_{IL} = LOW
I_{CCZ}	Power Supply Current		160	190	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

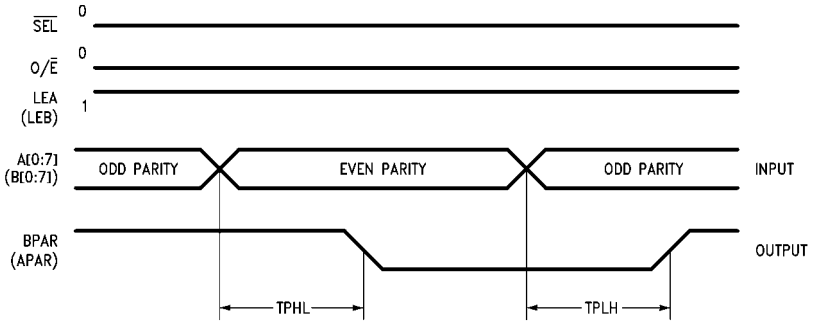
Symbol	Parameter	T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			T_A = 0°C to +70°C, V_{CC} = +5.0V, C_L = 50 pF		Units	Figure Number
		Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	4.0	7.5	13.0	4.0	14.0	ns	Figure 1
t_{PHL}	A_n, APAR to B_n, BPAR	4.0	8.5	13.0	4.0	14.0		
t_{PLH}	Propagation Delay	7.5	12.0	17.0	7.5	18.0	ns	Figure 2
t_{PHL}	A_n, B_n to BPAR, APAR	7.5	12.5	17.0	7.5	18.0		
t_{PLH}	Propagation Delay	7.5	12.0	17.0	7.5	18.0	ns	Figure 3
t_{PHL}	A_n, B_n to $\overline{ERRA}$, $\overline{ERRB}$	7.5	12.5	17.0	7.5	18.0		
t_{PLH}	Propagation Delay	4.5	7.5	11.0	4.5	12.0	ns	Figure 4
t_{PHL}	ODD/$\overline{EVEN}$ to $\overline{ERRA}$, $\overline{ERRB}$	4.5	8.0	11.0	4.5	12.0		
t_{PLH}	Propagation Delay	4.5	7.5	11.5	4.5	12.5	ns	Figure 5
t_{PHL}	ODD/$\overline{EVEN}$ to APAR, BPAR	4.5	8.5	11.5	4.5	12.5		
t_{PLH}	Propagation Delay	5.5	9.0	13.0	5.5	14.0	ns	Figure 6
t_{PHL}	APAR, BPAR to $\overline{ERRA}$, $\overline{ERRB}$	5.5	9.5	13.0	5.5	14.0		
t_{PLH}	LEA/LEB to	9.5	13.0	17.5	7.5	18.0	ns	Figure 7
t_{PHL}	$\overline{ERRA}$ /$\overline{ERRB}$	9.7		17.5	7.5	18.0		
t_{PLH}	Propagation Delay	3.0	6.0	10.0	3.0	11.0	ns	Figure 10
t_{PHL}	$\overline{SEL}$ to APAR, BPAR	3.0	7.0	10.0	3.0	11.0		
t_{PLH}	Propagation Delay	3.5	7.0	10.0	3.5	11.0	ns	Figure 11
t_{PHL}	LEB to A_n, APAR	3.5	8.0	10.0	3.5	11.0		
t_{PLH}	Propagation Delay	3.5	6.5	10.0	3.5	11.0	ns	Figure 11
t_{PHL}	LEA to B_n, BPAR	3.5	7.5	10.0	3.5	11.0		
t_{PZH}	Output Enable Time	1.0	4.5	10.0	1.0	11.0	ns	Figure 8, Figure 9
t_{PZL}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.0	6.5	10.0	1.0	11.0		
	APAR or B_n, BPAR							
t_{PHZ}	Output Disable Time	1.0	4.0	7.0	1.0	8.0	ns	Figure 8, Figure 9
t_{PLZ}	$\overline{GBA}$ or $\overline{GAB}$ to A_n,	1.0	4.0	7.0	1.0	8.0		
	APAR or B_n, BPAR							
t_S(H)	Setup Time, HIGH or LOW	5.0	1.6		5.0		ns	Figure 12, Figure 13
t_S(L)	A_n, B_n to LEA, LEB	5.0	1.8		5.0			
t_H(H)	Hold Time, HIGH or LOW	0	–1.7		0		ns	Figure 12, Figure 13
t_H(L)	A_n, B_n to LEA, LEB	0	–1.5		0			
t_W	Pulse Width for LEA, LEB	6.0	2.0		6.0		ns	Figure 14

AC Path



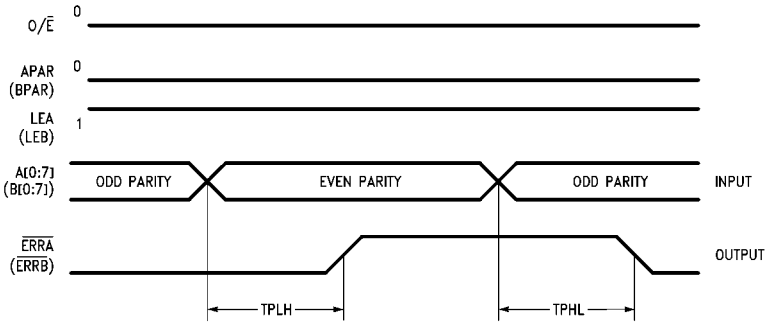
A_n, APAR → B_n, BPAR
(B_n, BPAR → A_n, APAR)

FIGURE 1.



A_n → BPAR
(B_n → APAR)

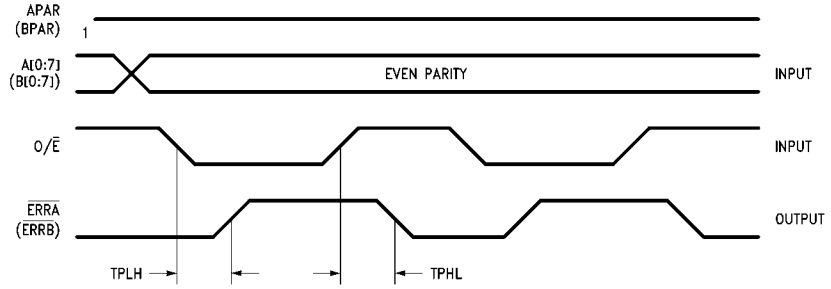
FIGURE 2.



A_n → $\overline{ERRA}$
(B_n → $\overline{ERRB}$)

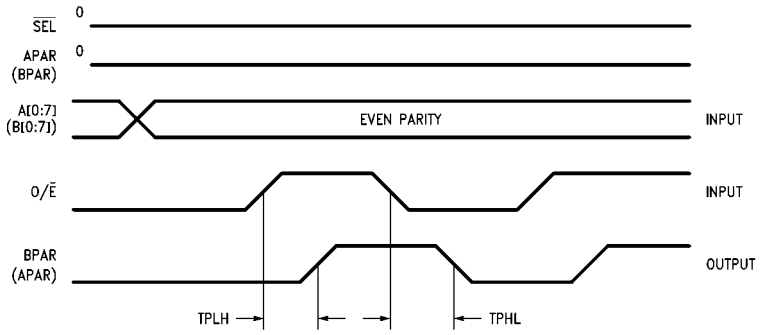
FIGURE 3.

AC Path (Continued)



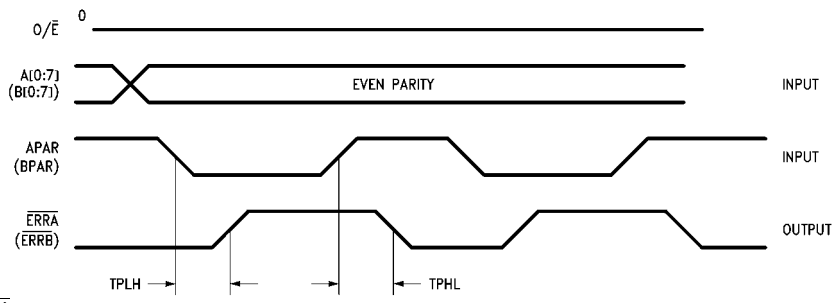
O/$\overline{E}$ → $\overline{ERRA}$
O/$\overline{E}$ → $\overline{ERRB}$

FIGURE 4.



O/$\overline{E}$ → BPAR
(O/$\overline{E}$ → APAR)

FIGURE 5.



APAR → $\overline{ERRA}$
(BPAR → $\overline{ERRB}$)

FIGURE 6.

AC Path (Continued)

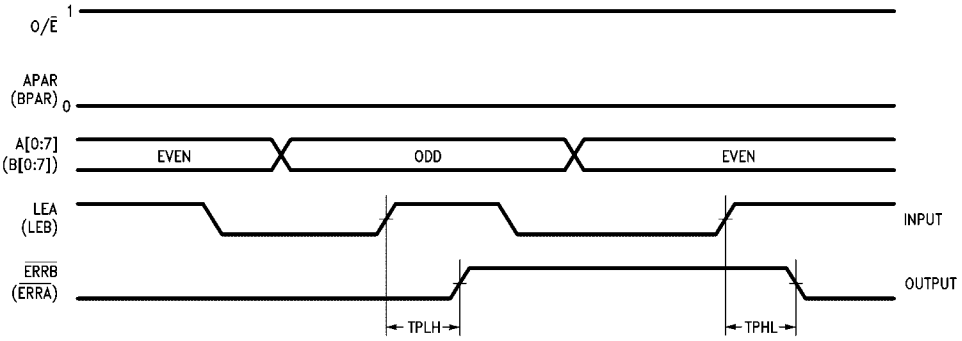
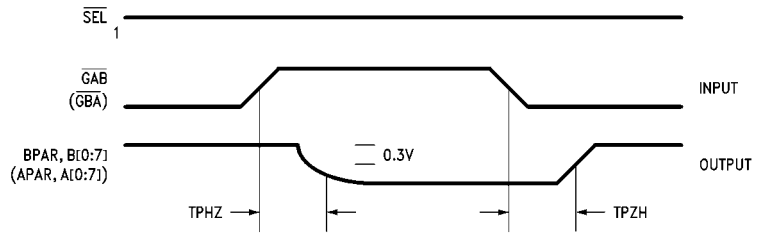
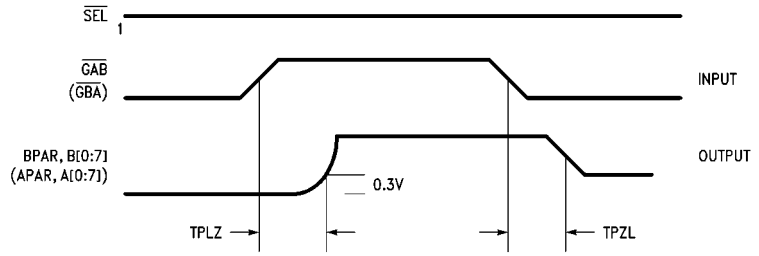


FIGURE 7.



ZH, HZ

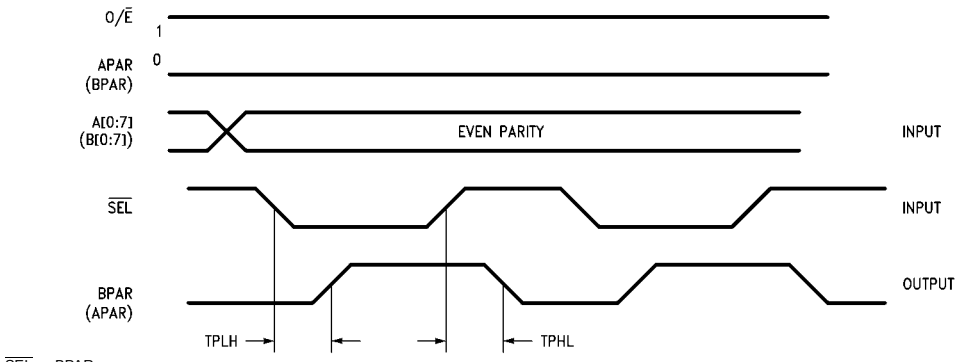
FIGURE 8.



ZL, LZ

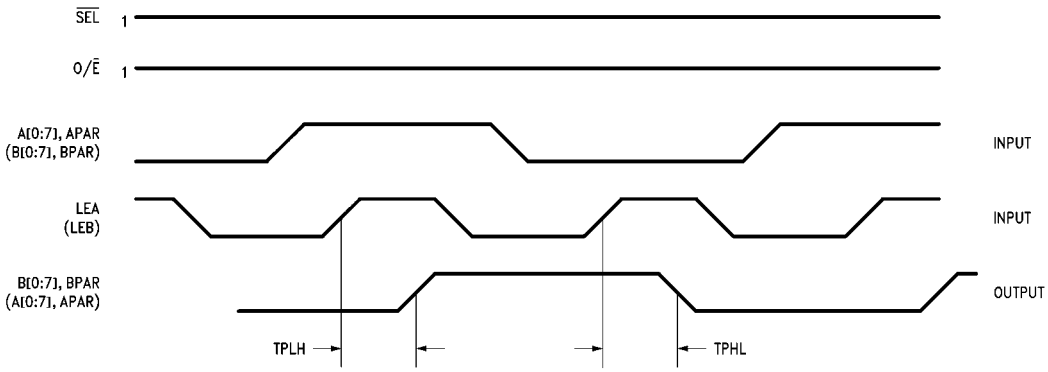
FIGURE 9.

AC Path (Continued)



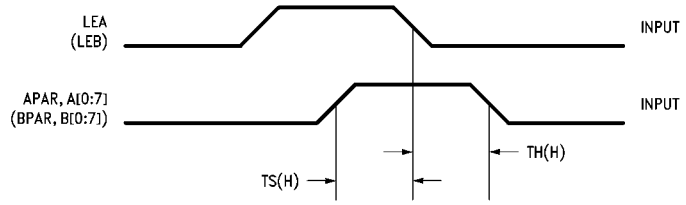
SEL → BPAR
(SEL → APAR)

FIGURE 10.



LEA → BPAR, B[0:7]
(LEB → APAR, A[0:7])

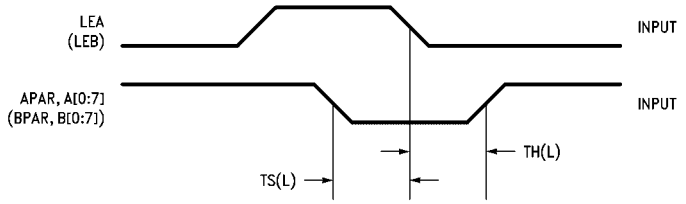
FIGURE 11.



TS(H), TH(H)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 12.

AC Path (Continued)



TS(L), TH(L)
LEA → APAR, A[0:7]
(LEB → BPAR, B[0:7])

FIGURE 13.

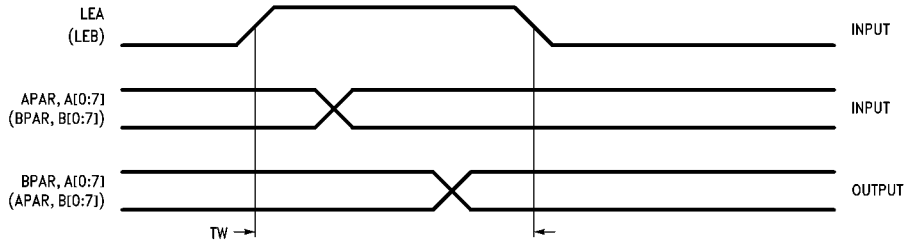
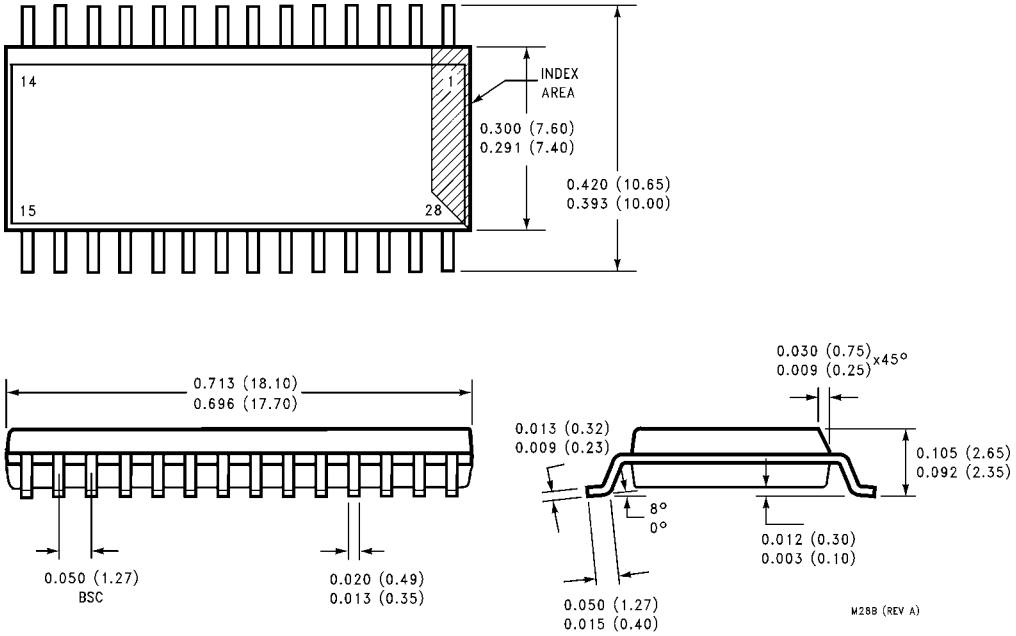


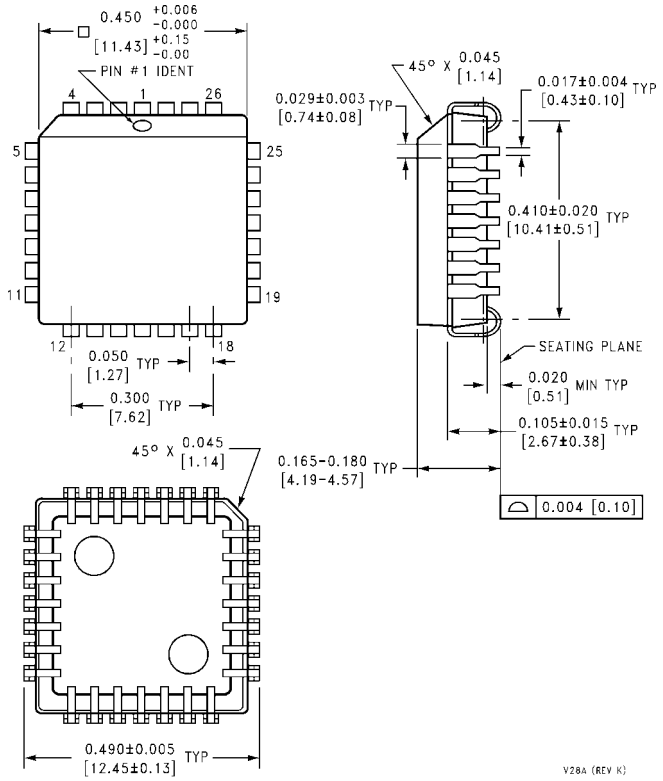
FIGURE 14.

Physical Dimensions inches (millimeters) unless otherwise noted



28-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M28B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



28-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.450 Square
Package Number V28A

National Semiconductor

March 1993

54FCT/74FCT240
Inverting Octal Buffer/Line Driver with TRI-STATE® Outputs

General Description

The 'FCT240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

FACT™ FCT utilizes NSC quiet series technology to provide improved quiet output switching and dynamic threshold performance.

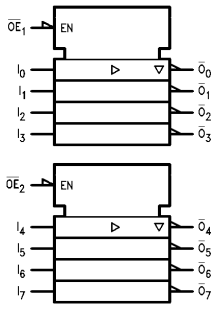
FACT FCT features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- I_{CC} and I_{OZ} reduced to 40.0 μA and $\pm$2.5 μA respectively
- NSC 54FCT/74FCT240 is pin and functionally equivalent to IDT 54FCT/74FCT240
- Inverting TRI-STATE outputs
- Input clamp diodes to limit bus reflections
- TTL/CMOS input and output level compatible
- I_{OL} = 64 mA (commercial), 48 mA (military)
- CMOS power levels
- ESD immunity $\geq$ 4 kV typ
- Military product compliant to MIL-STD 883 and standard military drawing #5962-87655

Logic Symbol

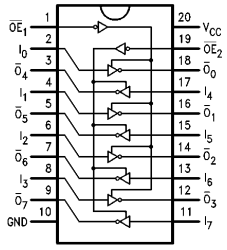
IEEE/IEC



TL/F/10239–1

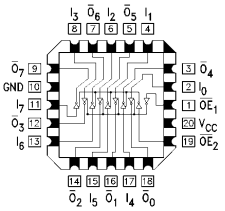
Connection Diagrams

Pin Assignment for DIP, Flatpak and SOIC



TL/F/10239–2

Pin Assignment for LCC



TL/F/10239–3

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	TRI-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Table

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}1$	I	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}2$	I	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Terminal Voltage with Respect to GND (V_{TERM})
- 74FCT: −0.5V to +7.0V
- 54FCT: −0.5V to +7.0V

Temperature under Bias (T_{BIAS})
- 74FCT: −55°C to +125°C
- 54FCT: −65°C to +135°C

Storage Temperature (T_{STG})
- 74FCT: −55°C to +125°C
- 54FCT: −65°C to +150°C

DC Output Current (I_{OUT}): 120 mA

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. Exposure to absolute maximum rating conditions for extended periods may affect reliability. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables.

Recommended Operating Conditions

Supply Voltage (V_{CC})
- 54FCT: 4.5V to 5.5V
- 74FCT: 4.75V to 5.25V

Input Voltage: 0V to V_{CC}

Output Voltage: 0V to V_{CC}

Operating Temperature (T_A)
- 54FCT: −55°C to +125°C
- 74FCT: −0°C to +70°C

Junction Temperature (T_J)
- CDIP: 175°C
- PDIP: 140°C

Note: All commercial packaging is not recommended for applications requiring greater than 2000 temperature cycles from −40°C to +125°C.

DC Characteristics for 'FCT Family Devices

Typical values are at V_{CC} = 5.0V, 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com: V_{CC} = 5.0V ±5%, T_A = 0°C to +70°C; Mil: V_{CC} = 5.0V ±10%, T_A = −55°C to +125°C, $V_{HC} = V_{CC} - 0.2V$.

Symbol	Parameter	54FCT/74FCT Min	54FCT/74FCT Typ	54FCT/74FCT Max	Units	Conditions	
V_{IH}	Minimum High Level Input Voltage	2.0			V		
V_{IL}	Maximum Low Level Input Voltage			0.8	V		
I_{IH}	Input High Current			5.0 5.0	μA	V_{CC} = Max	$V_I = V_{CC}$ V_I = 2.7V (Note 2)
I_{IL}	Input Low Current			−5.0 −5.0	μA	V_{CC} = Max	V_I = 0.5V (Note 2) V_I = GND
I_{OZ}	Maximum TRI-STATE Current			2.5 2.5 −2.5 −2.5	μA	V_{CC} = Max	$V_O = V_{CC}$ V_O = 2.7V (Note 2) V_O = 0.5V (Note 2) V_O = GND
V_{IK}	Clamp Diode Voltage		−0.7	−1.2	V	V_{CC} = Min; I_N = −18 mA	
I_{OS}	Short Circuit Current	−60	−120		mA	V_{CC} = Max (Note 1); V_O = GND	
V_{OH}	Minimum High Level Output Voltage	2.8	3.0		V	V_{CC} = 3V; V_{IN} = 0.2V or V_{HC}; I_{OH} = −32 μA	
		V_{HC} 2.4 2.4	V_{CC} 4.3 4.3			V_{CC} = Min $V_{IN} = V_{IH}$ or V_{IL}	I_{OH} = −300 μA I_{OH} = −12 mA (Mil) I_{OH} = −15 mA (Com)
V_{OL}	Maximum Low Level Output Voltage		GND	0.2	V	V_{CC} = 3V; V_{IN} = 0.2V or V_{HC}; I_{OL} = 300 μA	
			GND 0.3 0.3	0.2 0.55 0.55		V_{CC} = Min $V_{IN} = V_{IH}$ or V_{IL}	I_{OL} = 300 μA I_{OL} = 48 mA (Mil) I_{OL} = 64 mA (Com)
I_{CC}	Maximum Quiescent Supply Current		1.0	40.0	μA	V_{CC} = Max $V_{IN} \geq V_{HC}$, $V_{IN} \leq 0.2V$ f_I = 0	
ΔI_{CC}	Quiescent Supply Current; TTL Inputs HIGH		0.5	2.0	mA	V_{CC} = Max V_{IN} = 3.4V (Note 3)	

DC Characteristics for 'FCT Family Devices (Continued)

Typical values are at $V_{CC} = 5.0V$, 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com: $V_{CC} = 5.0V \pm 5\%$, $T_A = 0°C$ to $+70°C$; Mil: $V_{CC} = 5.0V \pm 10\%$, $T_A = -55°C$ to $+125°C$, $V_{HC} = V_{CC} - 0.2V$.

Symbol	Parameter	74FCT			Units	Conditions	
		Min	Typ	Max			
I_{CCD}	Dynamic Power Supply Current (Note 4)		0.25	0.55	mA/MHz	V_{CC} = Max Outputs Open $\overline{OE}_1 = \overline{OE}_2$ = GND One Input Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
I_C	Total Power Supply Current (Note 6)		1.5	5.0	mA	V_{CC} = Max Outputs Open $\overline{OE}_1 = \overline{OE}_2$ = GND f_I = 10 MHz One Bit Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			1.8	6.0			V_{IN} = 3.4V V_{IN} = GND
			3.0	8.0		(Note 5) V_{CC} = Max Outputs Open $\overline{OE}_1 = \overline{OE}_2$ = GND f_I = 2.5 MHz Eight Bits Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			5.0	14.5			V_{IN} = 3.4V V_{IN} = GND

Note 1: Maximum test duration not to exceed one second, not more than one output shorted at one time.

Note 2: This parameter guaranteed but not tested.

Note 3: Per TTL driven input ($V_{IN} = 3.4V$); all other inputs at V_{CC} or GND.

Note 4: This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

Note 5: Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

Note 6: $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input ($V_{IN} = 3.4V$)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_I = Input Frequency

N_I = Number of Inputs at f_I

All currents are milliamps and all frequencies are in megahertz.

Note 7: For 54FCT, $I_{CCD} = 0.40$ mA/MHz.

Refer to applicable standard military drawing or NSC Table I for test conditions and I_C/I_{CC} limits.

AC Electrical Characteristics

Symbol	Parameter	54FCT/74FCT	74FCT		54FCT		Units
		$T_A = +25°C$ $V_{CC} = 5.0V$	$T_A, V_{CC} = Com$ $R_L = 500\Omega$ $C_L = 50$ pF		$T_A, V_{CC} = Mil$ $R_L = 500\Omega$ $C_L = 50$ pF		
		Typ	Min (Note 1)	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay D_n to O_n	5.0	1.5	8.0	1.5	9.0	ns
t_{PZH} t_{PZL}	Output Enable Time	7.0	1.5	10.0	1.5	10.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time	6.0	1.5	9.5	1.5	12.5	ns

Note 1: Minimum limits are guaranteed but not tested on propagation delays.

Capacitance $T_A = +25°C$, f = 1.0 MHz

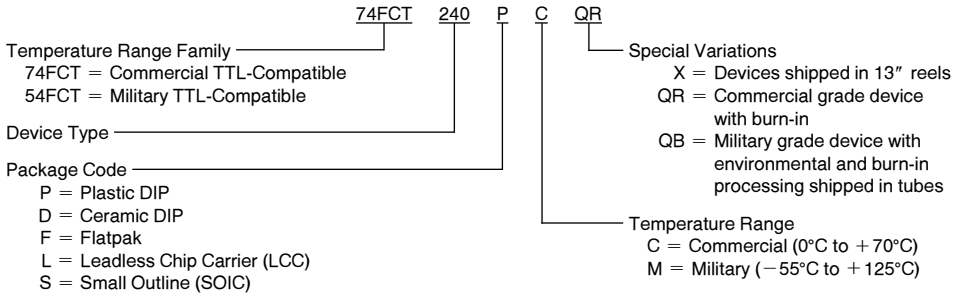
Symbol	Parameter (Note)	Typ	Max	Units	Condition
C_{IN}	Input Capacitance	6	10	pF	$V_{IN} = 0V$
C_{OUT}	Output Capacitance	8	12	pF	$V_{OUT} = 0V$

Note: This parameter is measured at characterization but not tested.

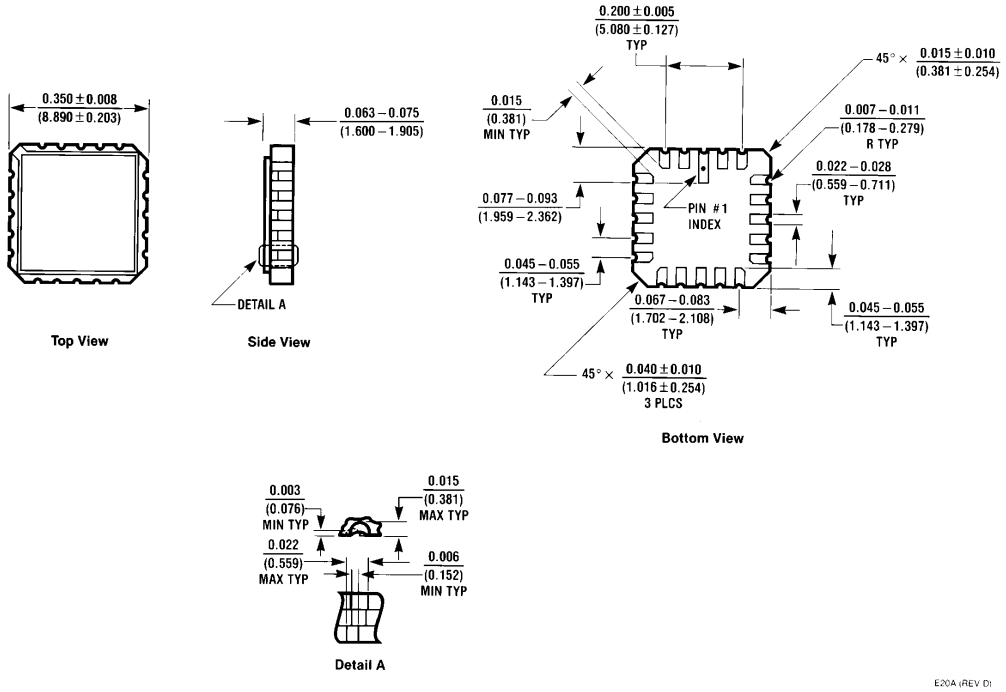
C_{OUT} for 74FCT only.

Ordering Information

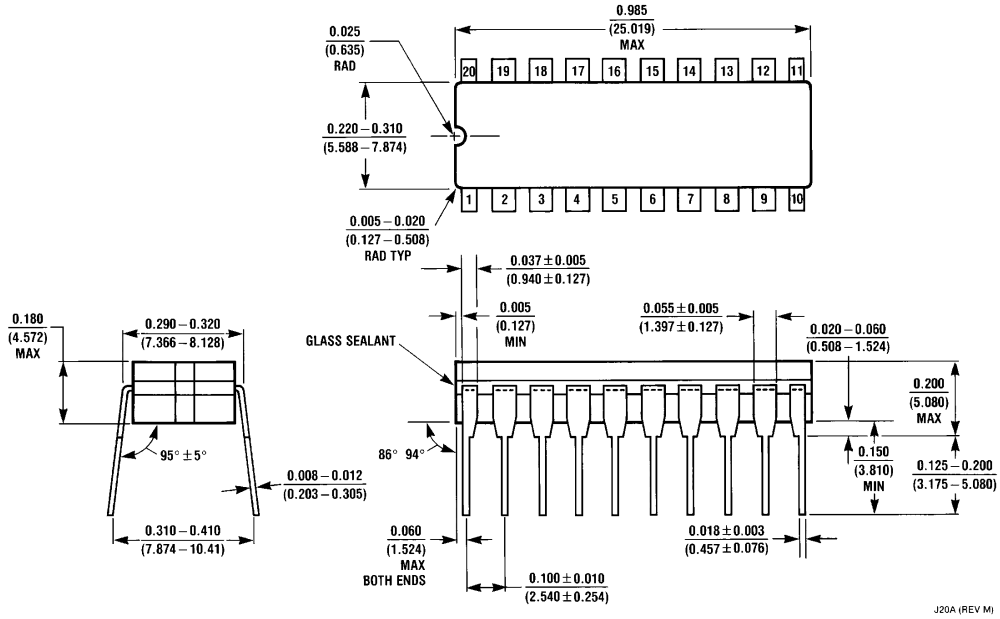
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)

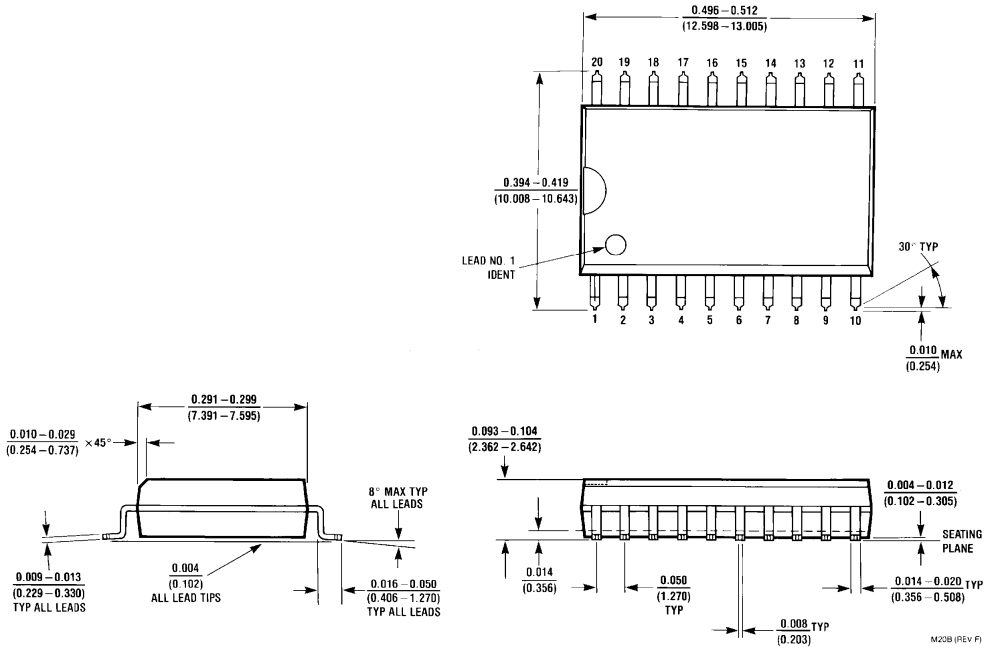


20-Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

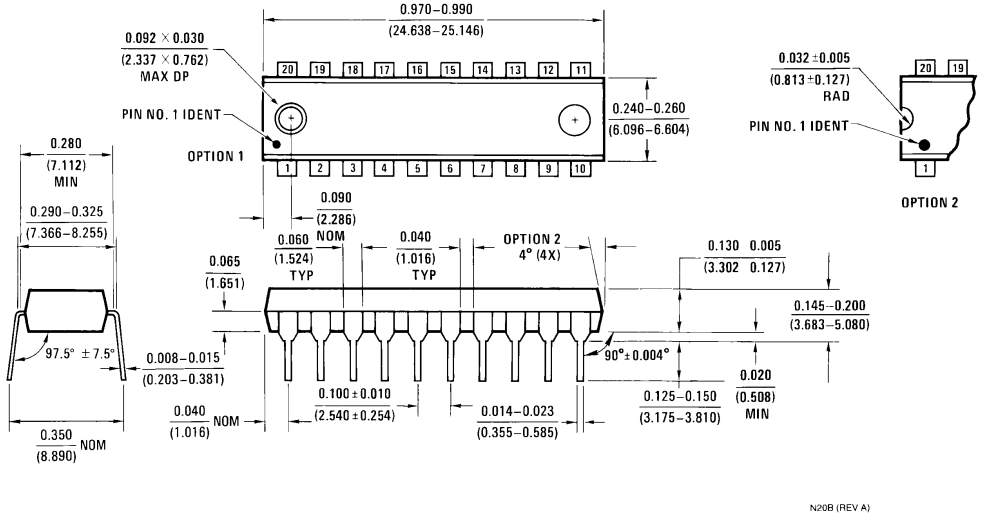


20-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J20A

Physical Dimensions inches (millimeters) (Continued)



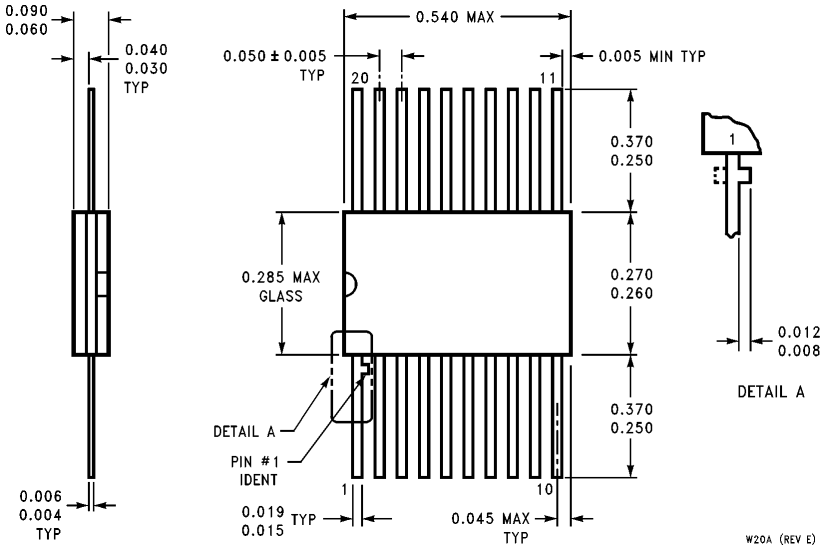
20-Lead Small Outline Integrated Circuit (S)
NS Package Number M20B



20-Lead Plastic Dual-In-Line Package (P)
NS Package Number N20B

Physical Dimensions inches (millimeters) (Continued)

Lit. # 114695



20-Lead Ceramic Flatpak (F)
NS Package Number W20A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

March 1993

54FCT/74FCT273
Octal D Flip-Flop

General Description

The 'FCT273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) input load and reset (clear) all flip-flops simultaneously.

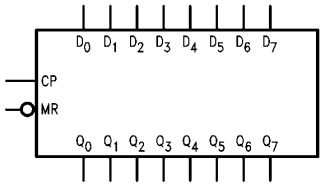
The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

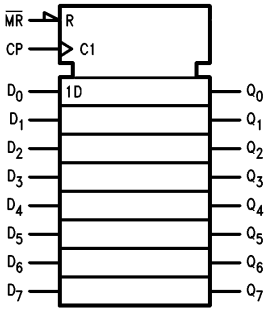
- I_{CC} reduced to 40.0 μA
- Ideal buffer for MOS microprocessor or memory
- Eight edge-triggered D flip-flops
- Buffered common clock
- Buffered, asynchronous master reset
- TTL input and output level compatible
- TTL levels accept CMOS levels
- I_{OL} = 48 mA (Com), 32 mA (Mil)
- NSC 54/74FCT273 is pin and functionally equivalent to IDT 54/74FCT273
- Military product compliant to MIL-STD-883 and Standard Military Drawing #5962-87656

Logic Symbols



TL/F/10146–1

IEEE/IEC

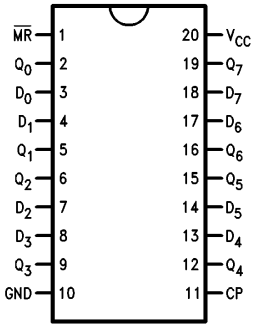


TL/F/10146–2

Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

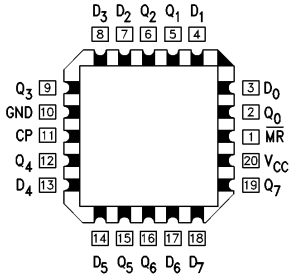
Connection Diagrams

Pin Assignment for DIP, Flatpak and SOIC



TL/F/10146–3

Pin Assignment for LCC



TL/F/10146–4

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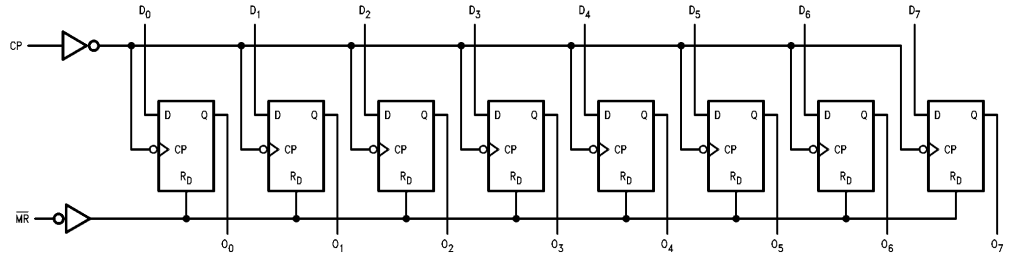
Mode Select-Function Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load '1'	H	⌐‾	H	H
Load '0'	H	⌐‾	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐‾ = LOW-to-HIGH Transition

Logic Diagram



TL/F/10146–5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Terminal Voltage with Respect to GND (V_{TERM})
- 54FCT: −0.5 to +7.0V
- 74FCT: −0.5 to +7.0V

Temperature Under Bias (T_{BIAS})
- 74FCT: −55°C to +125°C
- 54FCT: −65°C to +135°C

Storage Temperature (T_{STG})
- 74FCT: −55°C to +125°C
- 54FCT: −65°C to +150°C

DC Output Current (I_{OUT}): 120 mA

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ FCT circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})
- 54FCT: 4.5V to 5.5V
- 74FCT: 4.75 to 5.25V

Input Voltage: 0V to V_{CC}

Output Voltage: 0V to V_{CC}

Operating Temperature (T_A)
- 54FCT: −55°C to +125°C
- 74FCT: 0°C to +70°C

Junction Temperature (T_J)
- CDIP: 175°C
- PDIP: 140°C

Note: All commercial packaging is not recommended for applications requiring greater than 2000 temperature cycles from −40°C to +125°C.

DC Characteristics for 'FCT Family Devices

Typical values are at V_{CC} = 5.0V, 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com: V_{CC} = 5.0V ±5%, T_A = 0°C to +70°C; Mil: V_{CC} = 5.0V ±10%, T_A = −55°C to +125°C, V_{HC} = V_{CC} − 0.2V

Symbol	Parameter	54FCT/74FCT			Units	Conditions	
		Min	Typ	Max			
V_{IH}	Minimum High Level Input Voltage	2.0			V		
V_{IL}	Maximum Low Level Input Voltage			0.8	V		
I_{IH}	Input High Current			5.0 5.0	μA	V_{CC} = Max	V_I = V_{CC} V_I = 2.7V (Note 2)
I_{IL}	Input Low Current			−5.0 −5.0	μA	V_{CC} = Max	V_I = 0.5V (Note 2) V_I = GND
V_{IK}	Clamp Diode Voltage		−0.7	−1.2	V	V_{CC} = Min; I_N = −18 mA	
I_{OS}	Short Circuit Current	−60	−120		mA	V_{CC} = Max (Note 1); V_O = GND	
V_{OH}	Minimum High Level Output Voltage	2.8	3.0		V	V_{CC} = 3V; V_{IN} = 0.2V or V_{HC}; I_{OL} = −32 μA	
		V_{HC} 2.4 2.4	V_{CC} 4.3 4.3			V_{CC} = Min V_{IN} = V_{IH} or V_{IL}	I_{OH} = −300 μA I_{OH} = −12 mA (Mil) I_{OH} = −15 mA (Com)

DC Characteristics for 'FCT Family Devices (Continued)

Typical values are at $V_{CC} = 5.0V$, 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com: $V_{CC} = 5.0V \pm 5\%$, $T_A = 0°C$ to $+70°C$; Mil: $V_{CC} = 5.0V \pm 10\%$, $T_A = -55°C$ to $+125°C$, $V_{HC} = V_{CC} - 0.2V$

Symbol	Parameter	54FCT/74FCT			Units	Conditions	
		Min	Typ	Max			
V_{OL}	Maximum Low Level Output Voltage		GND	0.2	V	$V_{CC} = 3V$; $V_{IN} = 0.2V$ or V_{HC}; $I_{OL} = 300\ \mu A$	
			GND 0.3 0.3	0.2 0.5 0.5		V_{CC} = Min $V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 300\ \mu A$ $I_{OL} = 48$ mA (Mil) $I_{OL} = 32$ mA (Com)
I_{CC}	Maximum Quiescent Supply Current		1.0	40.0	μA	V_{CC} = Max $V_{IN} \geq V_{HC}$, $V_{IN} \leq 0.2V$ $f_I = 0$	
ΔI_{CC}	Quiescent Supply Current; TTL Inputs HIGH		0.5	2.0	mA	V_{CC} = Max $V_{IN} = 3.4V$ (Note 3)	
I_{CCD}	Dynamic Power Supply Current (Note 4)		0.25	0.40	mA/MHz	V_{CC} Max Outputs Open $\overline{MR} = V_{CC}$ One Input Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
V_H	Input Hysteresis on Clock Only		200		mV		
I_C	Total Power Supply Current (Note 6)		1.5	4.0	mA	V_{CC} = Max Outputs Open $\overline{MR} = V_{CC}$	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			1.8	6.0		$f_I = 10$ MHz One Bit Toggling 50% Duty Cycle	$V_{IN} = 3.4V$ V_{IN} = GND
			3.0	7.8		(Note 5) V_{CC} = Max Outputs Open $\overline{MR} = V_{CC}$	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			5.0	16.8		$f_I = 2.5$ MHz Eight Bits Toggling 50% Duty Cycle	$V_{IN} = 3.4V$ V_{IN} = GND
V_H	Input Hysteresis on Clock Only		200		mV		

Note 1: Maximum test duration not to exceed one second, not more than one output shorted at one time.

Note 2: This parameter guaranteed but not tested.

Note 3: Per TTL driven input ($V_{IN} = 3.4V$); all other inputs at V_{CC} or GND.

Note 4: This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

Note 5: Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

Note 6: $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Curent for a TTL High Input ($V_{IN} = 3.4V$)

D_H = Duty Cycle for TTL inputs High

N_T = Number of Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_I = Input Frequency

N_I = Number of Inputs at f_I

All currents are in milliamps and all frequencies are in megahertz.

AC Electrical Characteristics

Symbol	Parameter	54FCT/74FCT	74FCT		54FCT		Units
		$T_A = +25°C$ $V_{CC} = 5.0V$	$T_A, V_{CC} = Com$ $R_L = 500\Omega$ $C_L = 50$ pF		$T_A, V_{CC} = Mil$ $R_L = 500\Omega$ $C_L = 50$ pF		
		Typ	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay Clock to Output	7.0	2.0	13.0	1.5	9.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{MR}$ to Output	8.0	2.0	13.0	1.5	10.5	ns
t_{SU}	Setup Time HIGH or LOW Data to CP	1.5	3.0		3.5		ns
t_h	Hold Time HIGH or LOW Data to CP	1.0	2.0		2.0		ns
t_w	Clock Pulse Width HIGH or LOW	4.0	7.0		5.0		ns
t_w	$\overline{MR}$ Pulse Width HIGH or LOW	4.0	7.0		5.0		ns
t_{rec}	Recovery Time $\overline{MR}$ to CP	3.0	4.0		4.0		ns
f_{max}	Maximum Clock Frequency				90		MHz

Note 1: Minimum limits are guaranteed but not tested on Propagation Delays.

Capacitance $T_A = 25°C$, f = 1.0 MHz

Symbol	Parameter	Conditions	Typ	Max	Unit
C_{IN}	Input Capacitance	$V_{IN} = 0V$	6	10	pF
C_{OUT}	Output Capacitance	$V_{OUT} = 0V$	8	12	pF

Note: This parameter is guaranteed by characterization data and not tested.

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

74FCT 273 P C QR

Temperature Range Family
74FCT = Commercial TTL-Compatible
54FCT = Military TTL-Compatible

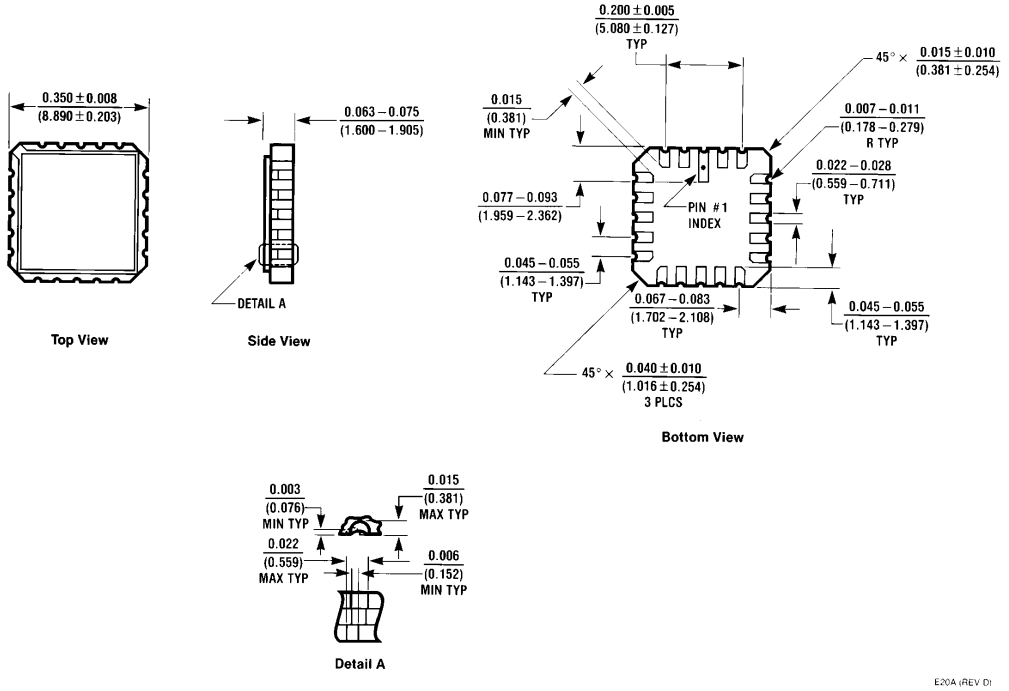
Device Type

Package Code
P = Plastic DIP
D = Ceramic DIP
F = Flatpak
L = Leadless Ceramic Chip Carrier (LCC)
S = Small Outline (SOIC)

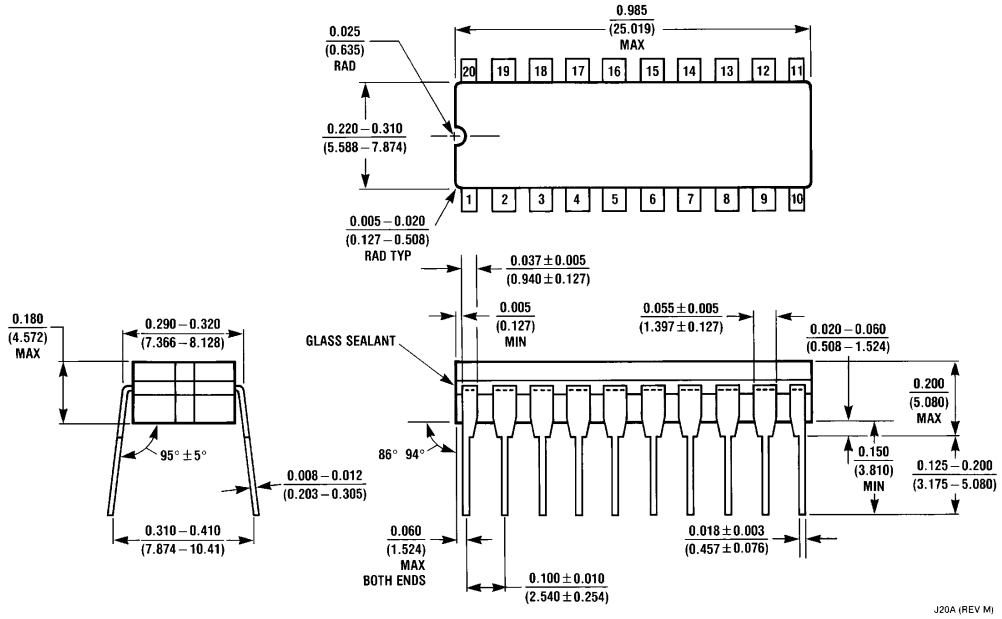
Special Variations
X = Devices shipped in 13″ reels
QR = Commercial grade device with burn-in
QB = Military grade with environmental and burn-in processing shipped in tubes.

Temperature Range
C = Commercial (0°C to +70°C)
M = Military (−55°C to +125°C)

Physical Dimensions inches (millimeters)

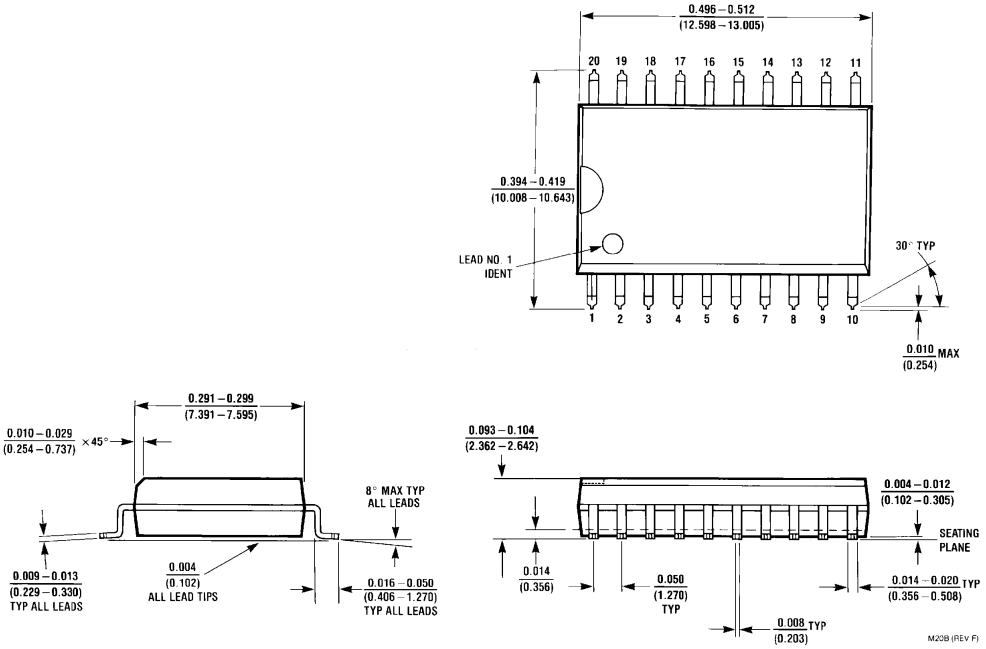


20-Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

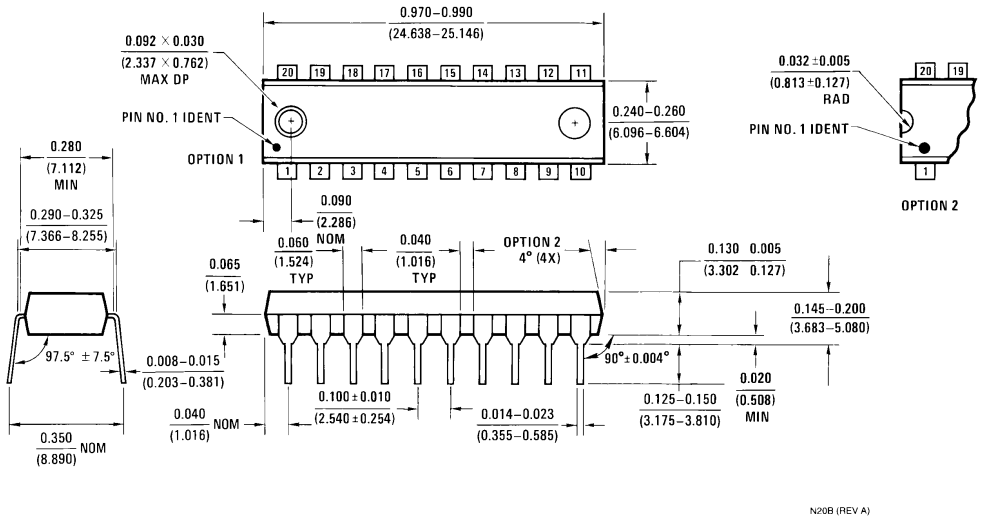


20-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J20A

Physical Dimensions inches (millimeters) (Continued)



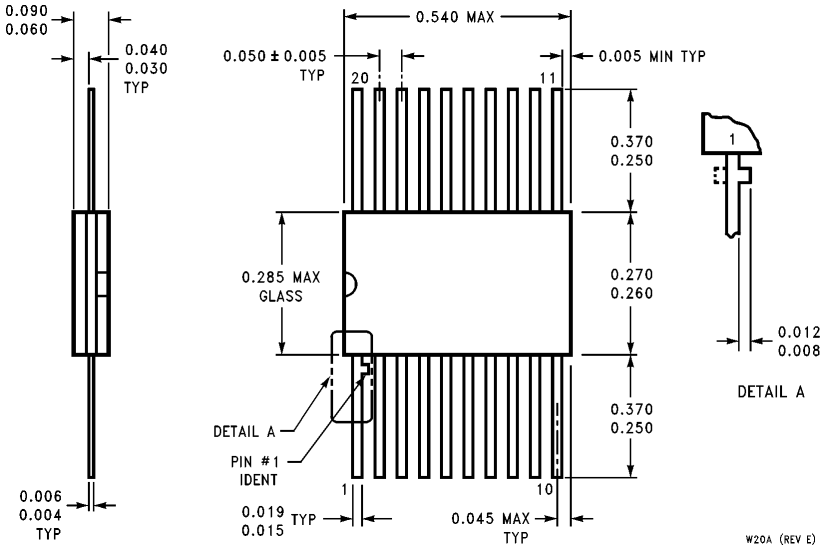
20-Lead Small Outline Integrated Circuit (S)
NS Package Number M20B



20-Lead Plastic Dual-In-Line Package (P)
NS Package Number N20B

Physical Dimensions inches (millimeters) (Continued)

Lit. # 114706



20-Lead Ceramic Flatpak (F)
NS Package Number W20A

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

April 1993

74FCT534
Octal D Flip-Flop with TRI-STATE® Outputs

General Description

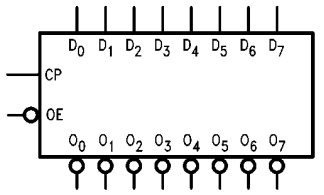
The 'FCT534 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and TRI-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops. FACT™ FCT utilizes NSC quiet series technology to provide improved quiet output switching and dynamic threshold performance.

FACT FCT features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance. The 'FCT534 is the same as the 'FCT374 except that the outputs are inverted.

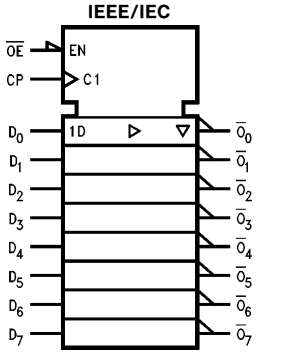
Features

- I_{CC} and I_{OZ} reduced to 40.0 μA and $\pm$2.5 μA respectively
- NSC 54/74FCT534 is pin and functionally equivalent to IDT 54/74FCT534
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Input clamp diodes to limit bus reflections
- TTL/CMOS input and output level compatible
- I_{OL} = 48 mA
- CMOS power levels
- ESD immunity $\geq$ 4 kV typ

Logic Symbols

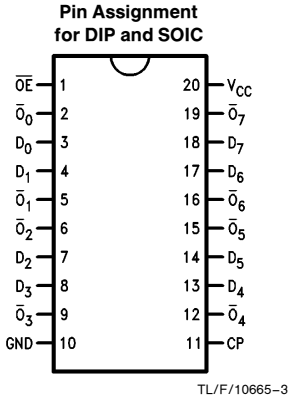


TL/F/10665–1



TL/F/10665–2

Connection Diagram



TL/F/10665–3

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	TRI-STATE Output Enable Input
$\overline{O}_0$–$\overline{O}_7$	Complementary TRI-STATE Outputs

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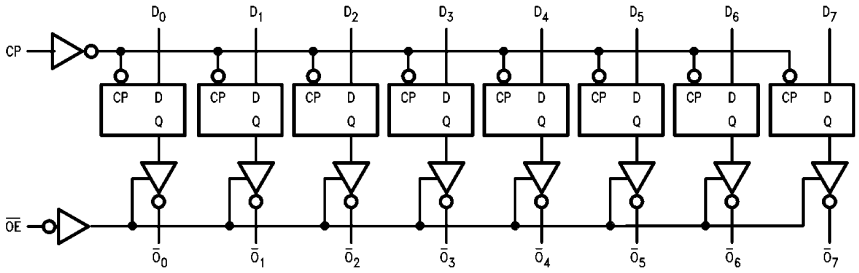
RRD-B30M105/Printed in U. S. A.

Functional Description

The 'FCT534 consists of eight edge-triggered flip-flops with individual D-type inputs and TRI-STATE complementary outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



TL/F/10665–5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Function Table

Inputs			Output
CP	**OE**	**D**	$\overline{\mathbf{O}}$
⌐‾	L	H	L
⌐‾	L	L	H
L	L	X	$\overline{O}_0$
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐‾ = LOW-to-HIGH Clock Transition
Z = High Impedance
$\overline{O}_0$ = Value stored from previous clock cycle

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Terminal Voltage with Respect to GND (V_{TERM})
74FCT −0.5V to +7.0V

Temperature Under Bias (T_{BIAS})
74FCT −55°C to +125°C

Storage Temperature (T_{STG})
74FCT −55°C to +125°C

DC Output Current (I_{OUT}) 120 mA

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. Exposure to absolute maximum rating conditions for extended periods may affect reliability. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables.

Recommended Operating Conditions

Supply Voltage (V_{CC})
74FCT 4.75V to 5.25V

Input Voltage 0V to V_{CC}

Output Voltage 0V to V_{CC}

Operating Temperature (T_A)
74FCT −0°C to +70°C

Junction Temperature (T_J)
PDIP 140°C

Note: All commercial packaging is not recommended for applications requiring greater than 2000 temperature cycles from −40°C to +125°C.

DC Characteristics for 'FCTA Family Devices

Typical values are at V_{CC} = 5.0V, 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com: V_{CC} = 5.0V ±5%, T_A = 0°C to +70°C; V_{HC} = V_{CC} − 0.2V.

Symbol	Parameter	74FCTA			Units	Conditions	
		Min	Typ	Max			
V_{IH}	Minimum High Level Input Voltage	2.0			V		
V_{IL}	Maximum Low Level Input Voltage			0.8	V		
I_{IH}	Input High Current			5.0 5.0	μA	V_{CC} = Max	V_I = V_{CC} V_I = 2.7V (Note 2)
I_{IL}	Input Low Current			−5.0 −5.0	μA	V_{CC} = Max	V_I = 0.5V (Note 2) V_I = GND
I_{OZ}	Maximum TRI-STATE Current			2.5 2.5 −2.5 −2.5	μA	V_{CC} = Max	V_O = V_{CC} V_O = 2.7V (Note 2) V_O = 0.5V (Note 2) V_O = GND
V_{IK}	Clamp Diode Voltage		−0.7	−1.2	V	V_{CC} = Min; I_N = −18 mA	
I_{OS}	Short Circuit Current	−60	−120		mA	V_{CC} = Max (Note 1); V_O = GND	
V_{OH}	Minimum High Level Output Voltage	2.8	3.0		V	V_{CC} = 3V; V_{IN} = 0.2V or V_{HC}; I_{OH} = −32 μA	
		V_{HC} 2.4	V_{CC} 4.3			V_{CC} = Min V_{IN} = V_{IH} or V_{IL}	I_{OH} = −300 μA I_{OH} = −15 mA
V_{OL}	Maximum Low Level Output Voltage		GND	0.2	V	V_{CC} = 3V; V_{IN} = 0.2V or V_{HC}; I_{OL} = 300 μA	
			GND 0.3	0.2 0.5		V_{CC} = Min V_{IN} = V_{IH} or V_{IL}	I_{OL} = 300 μA I_{OL} = 48 mA

DC Characteristics for 'FCT Family Devices (Continued)

Typical values are at V_{CC} = 5.0V, 25°C ambient and maximum loading. For test conditions shown as Max, use the value specified for the appropriate device type: Com: V_{CC} = 5.0V ±5%, T_A = 0°C to +70°C; V_{HC} = V_{CC} − 0.2V.

Symbol	Parameter	74FCT			Units	Conditions	
		Min	Typ	Max			
I_{CC}	Maximum Quiescent Supply Current		1.0	40.0	μA	V_{CC} = Max $V_{IN} \geq V_{HC}$, $V_{IN} \leq 0.2V$ f_I = 0	
ΔI_{CC}	Quiescent Supply Current; TTL Inputs HIGH		0.5	2.0	mA	V_{CC} = Max V_{IN} = 3.4V (Note 3)	
I_{CCD}	Dynamic Power Supply Current (Note 4)		0.15	0.25	mA/MHz	V_{CC} = Max Outputs Open $\overline{OE}$ = GND One Input Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
I_C	Total Power Supply Current (Note 6)		1.5	4.0	mA	V_{CC} = Max Outputs Open f_{CP} = 10 MHz $\overline{OE}$ = GND f_I = 5 MHz One Bit Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			1.8	6.0			V_{IN} = 3.4V V_{IN} = GND
			3.0	7.8		(Note 5) V_{CC} = Max Outputs Open $\overline{OE}$ = GND f_{CP} = 10 MHz f_I = 2.5 MHz Eight Bits Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq 0.2V$
			5.0	16.8			V_{IN} = 3.4V V_{IN} = GND
V_H	Input Hysteresis on Clock Only		200		mV		

Note 1: Maximum test duration not to exceed one second, not more than one output shorted at one time.

Note 2: This parameter guaranteed but not tested.

Note 3: Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.

Note 4: This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

Note 5: Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

Note 6: $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)

D_H = Duty Cycle for TTL inputs High

N_T = Number of Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_I = Input Frequency

N_I = Numbers of Inputs at f_I

All currents are in milliamps and all frequencies are in megahertz.

AC Electrical Characteristics

Symbol	Parameter	74FCT	74FCT		Units
		$T_A = +25°C$ $V_{CC} = 5.0V$	$T_A, V_{CC} =$ Com $C_L = 50$ pF		
		Typ	Min (Note 1)	Max	
t_{PLH} t_{PHL}	Propagation Delay C_P to $\overline{O}n$	6.5	1.5	10.0	ns
t_{PZH} t_{PZL}	Output Enable Time	9.0	1.5	12.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time	6.0	1.5	8.0	ns
t_s	Set Up Time High or Low Dn to CP	1.0	2.0		ns
t_h	Hold Time High or Low Dn to CP	0.5	1.5		ns
t_w	CP Pulse Width High or Low	4.0	7.0		ns

Note 1: Minimum limits guaranteed but not tested on propagation delays.

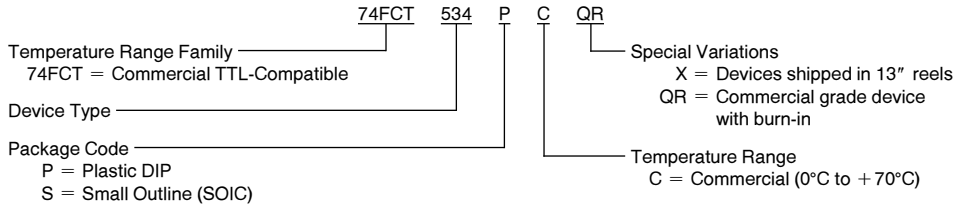
Capacitance $T_A = +25°C$, $f_I = 1.0$ MHz

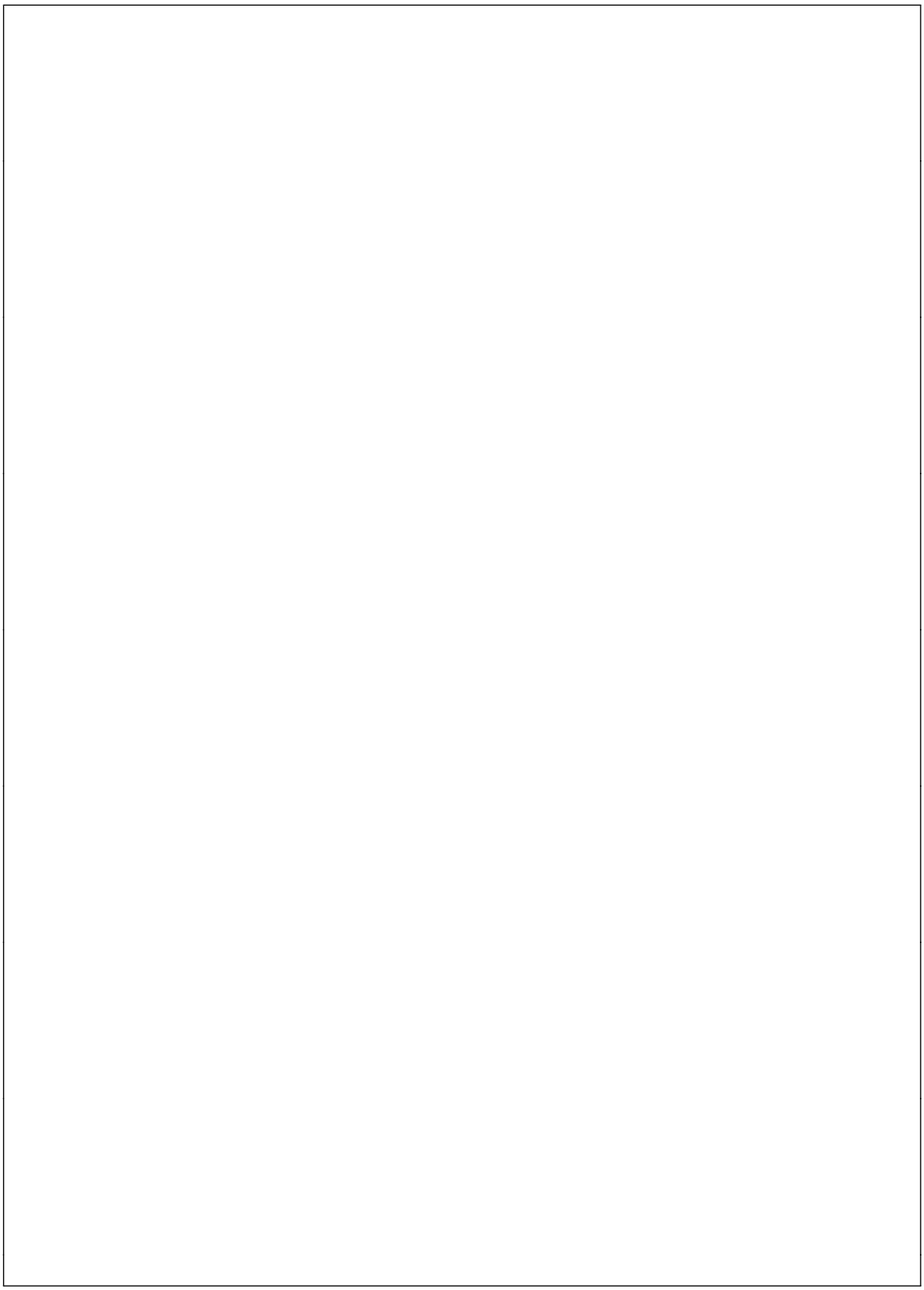
Symbol	Parameter	Typ	Max	Units	Conditions
C_{IN}	Input Capacitance	6	10	pF	$V_{IN} = 0V$
C_{OUT}	Output Capacitance	8	12	pF	$V_{OUT} = 0V$

Note: This parameter is measured at characterization but not tested.
C_{OUT} for 74FCT only.

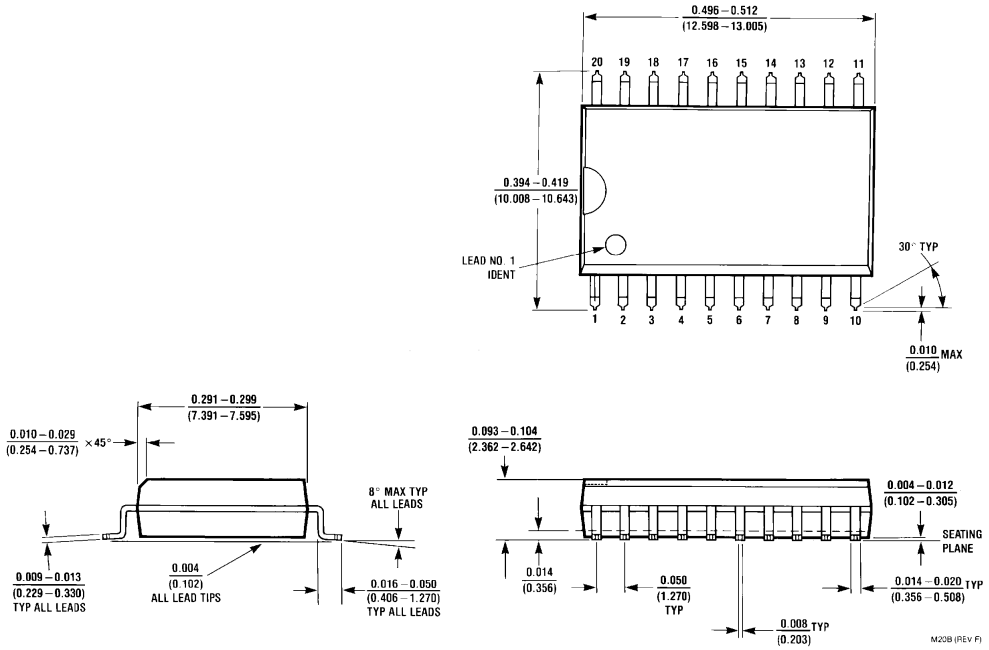
Ordering Information

The device number is used to form part of a simplified purchasing code where a package type and temperature range are defined as follows:



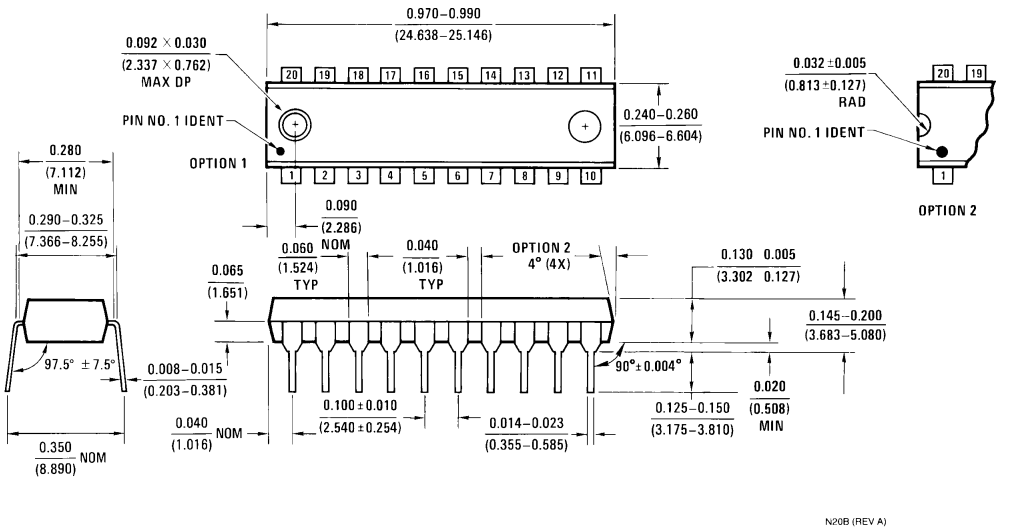


Physical Dimensions inches (millimeters)



20-Lead Small Outline Integrated Circuit (S)
NS Package Number M20B

Physical Dimensions inches (millimeters) (Continued)



20-Lead Plastic Dual-In-Line Package (P)
NS Package Number N20B

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1992
Revised August 1999

74FR74 • 74FR1074
Dual D-Type Flip-Flop

General Description

The 74FR74 and 74FR1074 are dual D-type flip-flops with true and complement (Q/$\overline{Q}$) outputs. On the 74FR74, data at the D inputs is transferred to the outputs on the rising edge of the clock input (CP_n). The 74FR1074 is the negative edge triggered version of this device. Both parts feature asynchronous clear (C_{Dn}) and set (S_{Dn}) inputs which are low level enabled.

Features

- 74FR74 is pin-for-pin compatible with the 74F74
- True 150 MHz f_{MAX} capability on 74FR74
- Outputs sink 24 mA and source 24 mA
- Guaranteed pin-to-pin skew specifications

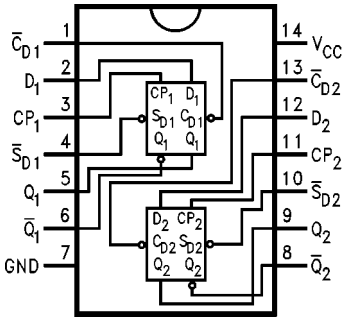
Ordering Code:

Order Number	Package Number	Package Description
74FR74SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74FR74PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
74FR1074SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74FR1074PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

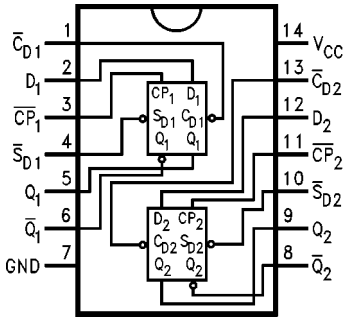
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

74FR74

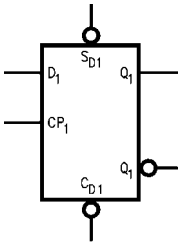


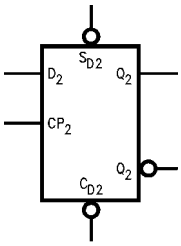
74FR1074



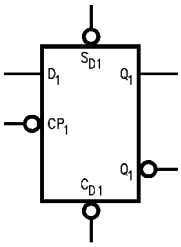
Logic Symbols

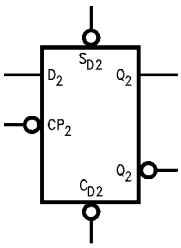
74FR74





74FR1074





Pin Descriptions

Pin Names	Description
D_n	Data Inputs
CP_n	Clock Inputs
S_{Dn}	Asynchronous Set Inputs
C_{Dn}	Asynchronous Clear Inputs
Q_n	True Output
$\overline{Q}_n$	Complementary Output

Truth Tables

74FR74

Inputs				Outputs	
$\overline{SD}$	$\overline{CD}$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	↗	H	H	L
H	H	↗	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
↗ = Rising Edge
Q_0 = Previous Q($\overline{Q}$) before LOW-to-HIGH Clock Transition

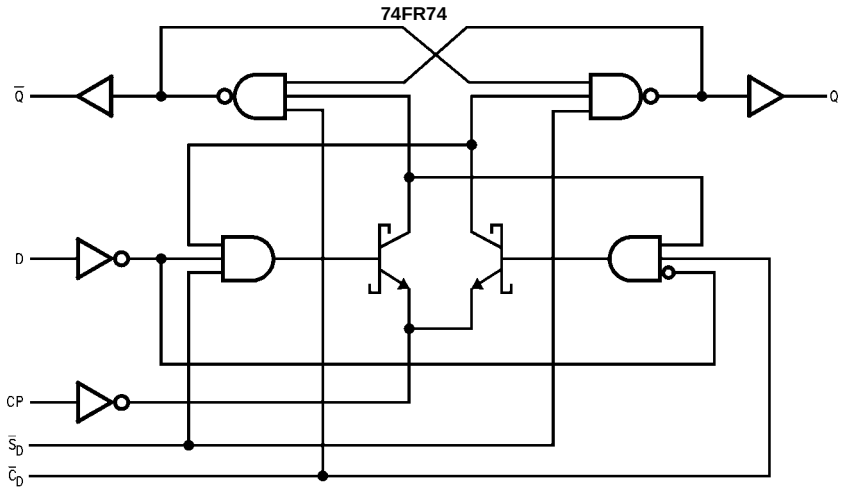
74FR1074

Inputs				Outputs	
$\overline{SD}$	$\overline{CD}$	$\overline{CP}$	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	↘	H	H	L
H	H	↘	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

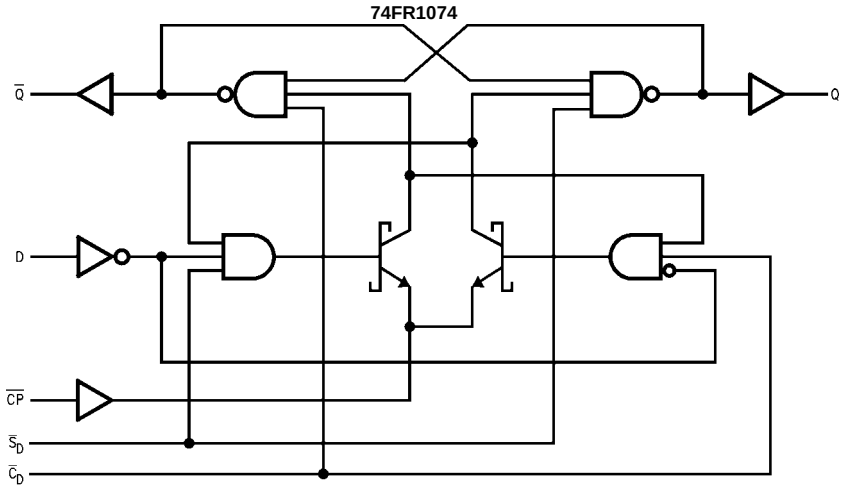
H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
↘ = Falling Edge
Q_0 = Previous Q($\overline{Q}$) before HIGH-to-LOW Clock Transition

Logic Diagrams

74FR74



74FR1074



Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	2000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.5			V	Min	I_{OH} = −1 mA
		2.4			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −24 mA
V_{OL}	Output LOW Voltage			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5V (D_n, CP_n)
				−1.8	mA	Max	V_{IN} = 0.5V (C_{Dn}, S_{Dn})
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Test			3.75	V	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
I_{OS}	Output Short-Circuit Current	−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{CC}	Power Supply Current			24	mA	Max	

AC Electrical Characteristics 74FR74

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150	190		150		MHz
t_{PLH} t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	2.5 2.5	3.5 4.5	5.0 6.0	2.5 2.5	5.0 6.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	1.5 2.0	3.5 5.5	5.5 7.0	1.5 2.0	5.5 7.0	ns
t_{OSHL} (Note 3)	Pin to Pin Skew for HL Transitions					1.0	ns
t_{OSLH} (Note 3)	Pin to Pin Skew for LH Transitions					1.0	ns
t_{OST} (Note 3)	Pin to Pin Skew for HL/LH Transitions					3.0	ns
$t_{Q/\overline{Q}}$ (Note 3)	True/Complement Output Skew					1.8	ns
t_{PS} (Note 3)	Pin (Signal) Transition Variation					1.8	ns

Note 3: Pin-to-Pin Skew is defined as the absolute value of the difference between the actual propagation delay for any outputs within the same packaged device. The specifications apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}) or in opposite directions both HL and LH (t_{OST}). t_{OST} is guaranteed by design.

AC Operating Requirements 74FR74

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW D_n to CP_n	2.5 2.5		2.5 2.5		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW D_n to CP_n	0 0		0 0		ns
$t_W(H)$ $t_W(L)$ (Note 4)	CP_n Pulse Width HIGH or LOW	3.3 3.3		3.3 3.3		ns
$t_W(L)$	$\overline{S}_{Dn}$ or $\overline{C}_{Dn}$ Pulse Width	4.0		4.0		ns
t_{REC}	Recovery Time $\overline{S}_{Dn}$ or $\overline{C}_{Dn}$ to CP_n	2.0		2.0		ns

Note 4: This specification is guaranteed by design.

AC Electrical Characteristics 74FR1074

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	120	160		120		MHz
t_{PLH} t_{PHL}	Propagation Delay CP_n to Q_n or $\overline{Q}_n$	2.5 3.0	4.0 5.0	5.5 6.5	2.5 3.0	5.5 6.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	1.5 2.0	3.5 5.5	5.5 7.0	1.5 2.0	5.5 7.0	ns
t_{OSHL} (Note 5)	Pin to Pin Skew for HL Transitions					1.5	ns
t_{OSLH} (Note 5)	Pin to Pin Skew for LH Transitions					1.5	ns
t_{OST} (Note 5)	Pin to Pin Skew for HL/LH Transitions					3.5	ns
$t_{Q/\overline{Q}}$ (Note 5)	True/Complement Output Skew					2.0	ns
t_{PS} (Note 5)	Pin (Signal) Transition Variation					2.0	ns

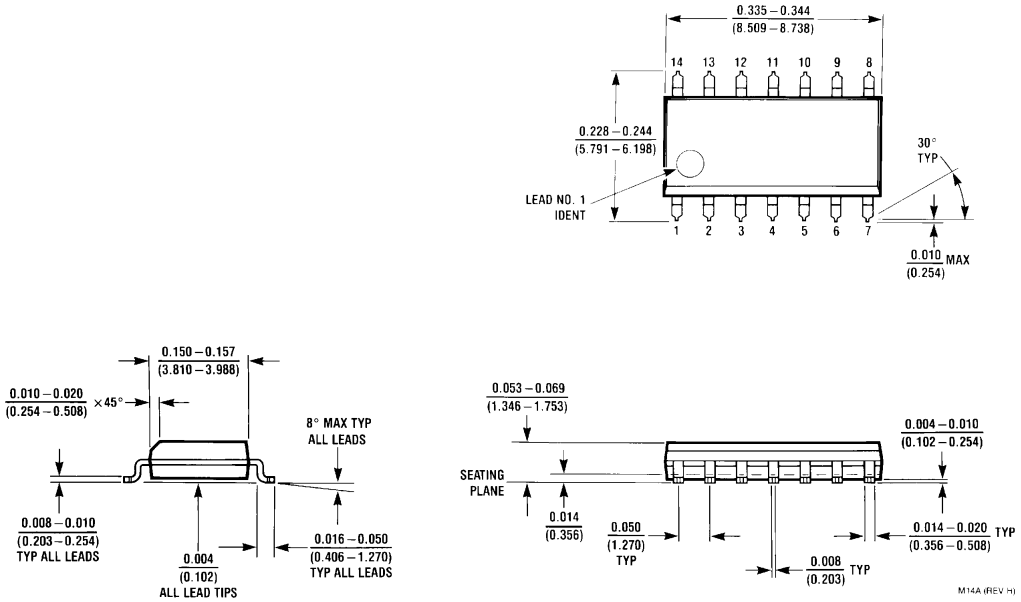
Note 5: Pin-to-Pin Skew is defined as the absolute value of the difference between the actual propagation delay for any outputs within the same packaged device. The specifications apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}) or in opposite directions both HL and LH (t_{OST}). t_{OST} is guaranteed by design.

AC Operating Requirements 74FR1074

Symbol	Parameter	$T_A = +25°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		$T_A = 0°C = +70°C$ $V_{CC} = +5.0V$ $C_L = 50$ pF		Units
		Min	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW D_n to CP_n	2.0 2.0		2.0 2.0		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW D_n to CP_n	0 0		0 0		ns
$t_W(H)$ $t_W(L)$ (Note 6)	$\overline{CP}_n$ Pulse Width HIGH or LOW	3.3 3.3		3.3 3.3		ns
$t_W(L)$	$\overline{S}_{Dn}$ or $\overline{C}_{Dn}$ Pulse Width	4.0		4.0		ns
t_{REC}	Recovery Time $\overline{S}_{Dn}$ or $\overline{C}_{Dn}$ to CP_n	2.0		2.0		ns

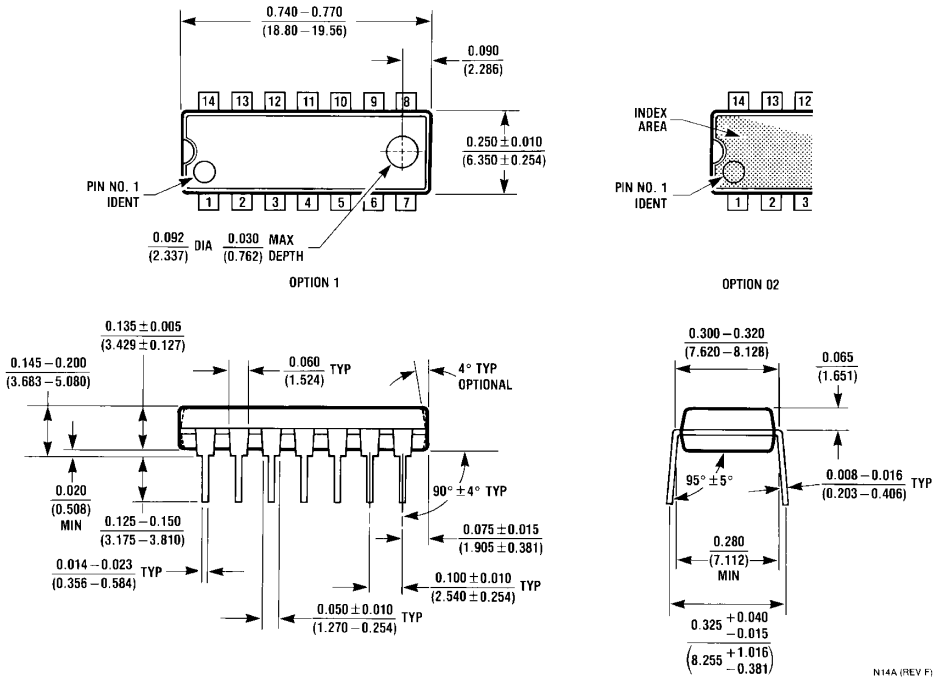
Note 6: This specification is guaranteed by design.

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

October 1989
Revised August 1999

74FR16245
16-Bit Transceiver with 3-STATE Outputs

General Description

The 74FR16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 64 mA on both the A and B Ports. The device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The transmit/receive ($T/\overline{R}_n$) inputs determine the direction of data flow through the transceiver. The output enable ($\overline{OE}_n$) inputs disable both A and B Ports by placing them in an high impedance state.

Features

- Non-inverting buffers
- Bidirectional data paths
- A and B output sink capability of 64 mA, source capability of 15 mA
- Separate control pins for each byte
- Guaranteed pin-to-pin skew
- Low 3-STATE I_{IL}
- 16-Bit version of the 74F245 or 74F645

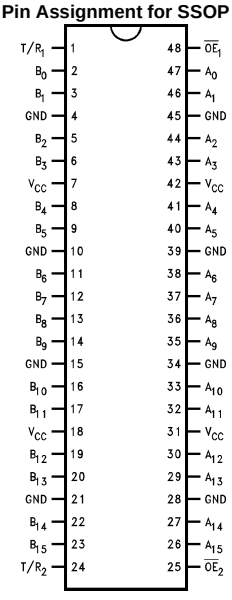
Ordering Code:

Order Number	Package Number	Package Description
74FR16245QC	V44A	44-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.650 Square
74FR16245SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide

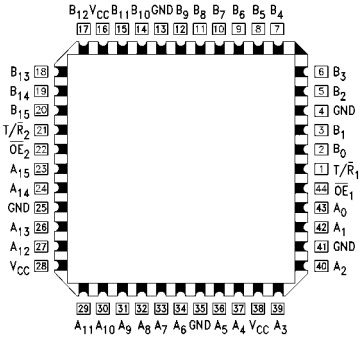
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

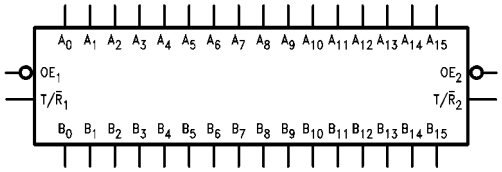
Pin Assignment for SSOP



Pin Assignment for PLCC



Logic Symbol



Pin Descriptions

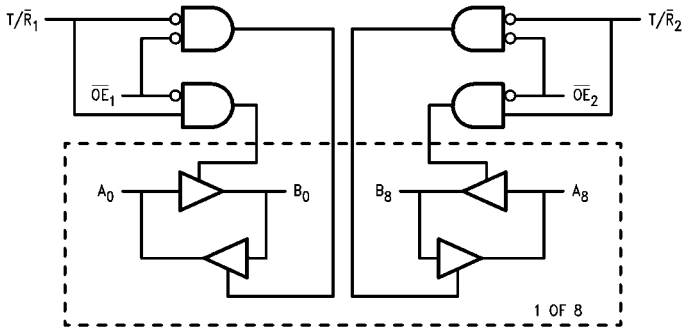
Pin Names	Description
$\overline{OE}_n$	Output Enable Input
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	A Bus Inputs/3-STATE Outputs
B_0–B_{15}	B Bus Inputs/3-STATE Outputs

Truth Table

Inputs				Output Operating Mode	
Byte1 (0:7)		Byte2 (8:15)			
$\overline{OE}_1$	$T/\overline{R}_1$	$\overline{OE}_2$	$T/\overline{R}_2$	Byte1 (0:7)	Byte2 (8:15)
L	L	H	X	Bus B Data to A	High Z State
L	H	H	X	Bus A Data to B	High Z State
H	X	L	L	High Z State	Bus B Data to A
H	X	L	H	High Z State	Bus A Data to B
L	L	L	L	Bus B Data to A	Bus B Data to A
L	H	L	H	Bus A Data to B	Bus A Data to B
H	X	H	X	High Z State	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	–65°C to +150°C
Ambient Temperature under Bias	–55°C to +125°C
Junction Temperature under Bias	–55°C to +150°C
V_{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
Input Voltage (Note 2)	–0.5V to +7.0V
Input Current (Note 2)	–30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	–0.5V to V_{CC}
3-STATE Output	–0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			–1.2	V	Min	I_{IN} = –18 mA
V_{OH}	Output HIGH Voltage	2.4 2.0	2.8 2.44		V	Min	I_{OH} = – 3 mA I_{OH} = – 15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage		0.45	0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Break-Down Test			7.0	µA	Max	V_{IN} = 7.0V ($\overline{OE}_n$, T/$\overline{R}_n$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			0.1	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			–150 –100	µA µA	Max Max	V_{IN} = 0.5V (T/$\overline{R}_n$, A_n, B_n) V_{IN} = 0.5V ($\overline{OE}_n$)
I_{OS}	Output Short-Circuit Current	–100		–225	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{IH} + I_{OZH}	Output Leakage Current		0	25	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current		–20	–150	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n)
I_{CCH}	Power Supply Current		70	105	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		127	165	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		71	105	mA	Max	V_O = HIGH Z
C_{IN}	Input Capacitance		8.0		pF	5.0	$\overline{OE}$, T/$\overline{R}$
			17.0		pF	5.0	A_n, B_n

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Unit
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.3	2.7	4.3	1.3	4.3	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.3	2.2	4.3	1.3	4.3	
t_{PZH}	Output Enable Time	3.9	6.9	13.9	3.9	13.9	ns
t_{PZL}		3.9	9.7	13.9	3.9	13.9	
t_{PHZ}	Output Disable Time	1.8	3.9	6.3	1.8	6.3	ns
t_{PLZ}		1.8	4.4	6.3	1.8	6.3	

Extended AC Characteristics

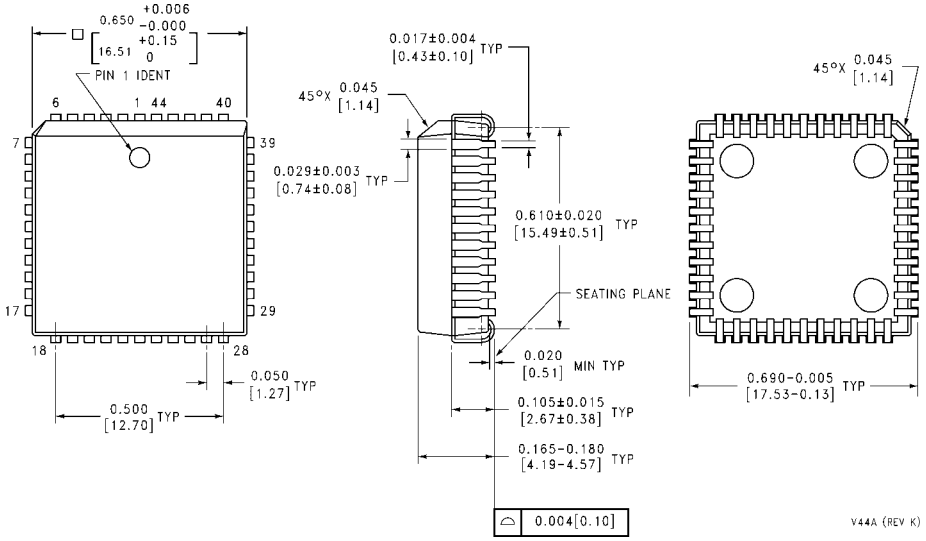
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, 16 Outputs Switching (Note 4)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 5)		Unit
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.3	5.8	3.2	8.2	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.3	5.8	3.2	8.2	
t_{PZH}	Output Enable Time	3.9	14.6			ns
t_{PZL}		3.9	14.6			
t_{PHZ}	Output Disable Time	1.8	6.3			ns
t_{PLZ}		1.8	6.3			
t_{OSHL} (Note 3)	Pin-to-Pin Skew for HL Transitions		1.2			ns
t_{OSLH} (Note 3)	Pin-to-Pin Skew for LH Transitions		2.2			ns
t_{OST} (Note 3)	Pin-to-Pin Skew for HL/LH Transitions		2.5			ns

Note 3: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}) LOW-to-HIGH (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Note 4: This specification is guaranteed but not tested The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

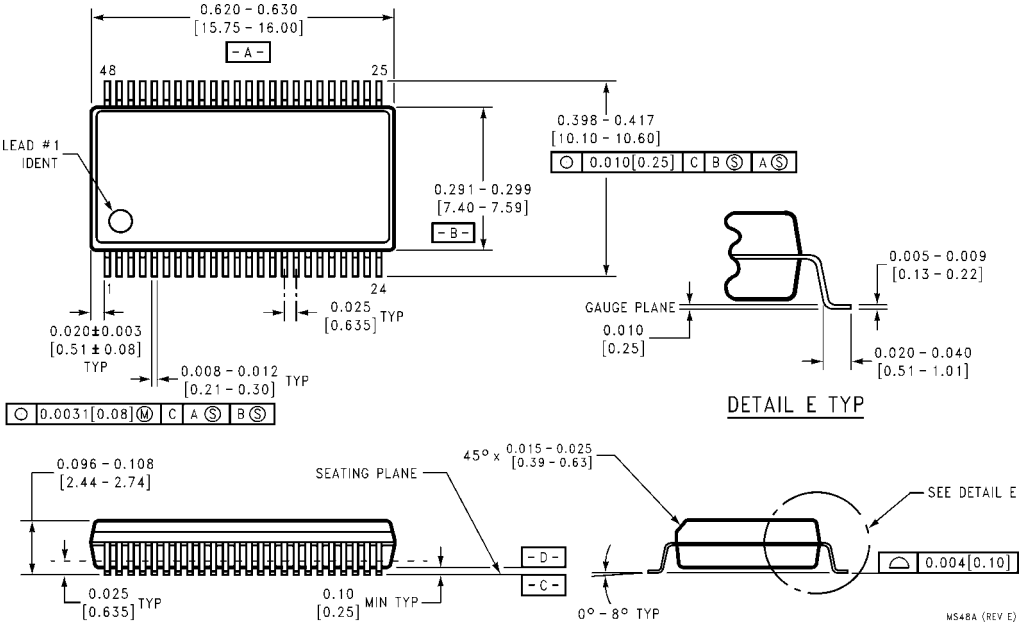
Note 5: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Physical Dimensions inches (millimeters) unless otherwise noted



44-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.650 Square
Package Number V44A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS48A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1989
Revised August 1999

74FR16540
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The 74FR16540 contains sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

Features

- Inverting buffers
- 3-STATE outputs drive bus lines
- Output sink capability of 64 mA, source capability of 15 mA
- Separate 3-STATE control pins for each byte
- Guaranteed 4000V minimum ESD protection
- Guaranteed multiple output switching, 250 pF delays and pin-to-pin skew
- 16-bit version of the 74F540, 74F240, or 74FR240

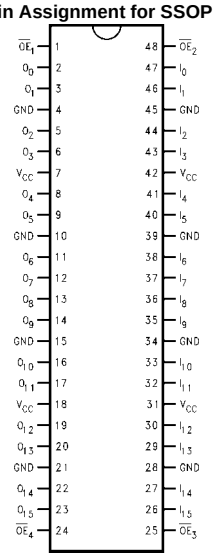
Ordering Code:

Order Number	Package Number	Package Description
74FR16540QC	V44A	44-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.650 Square
74FR16540SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide

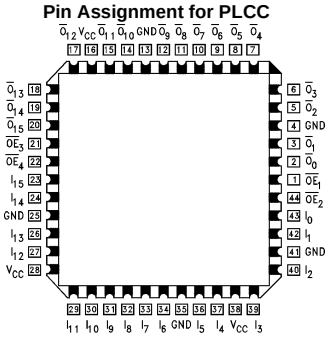
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

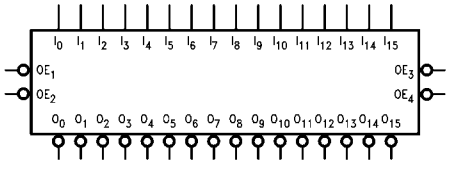
Pin Assignment for SSOP



Pin Assignment for PLCC



Logic Symbol



Pin Descriptions

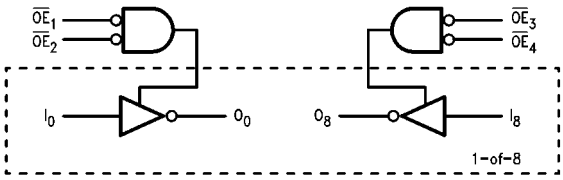
Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	3-STATE Outputs

Truth Table

Inputs						Outputs	
Byte1 [0:7]		Byte2 [8:15]		I_0–I_7 I_8–I_{15}		$\overline{O}_0$–$\overline{O}_7$	$\overline{O}_8$–$\overline{O}_{15}$
$\overline{OE}_1$	$\overline{OE}_2$	$\overline{OE}_3$	$\overline{OE}_4$				
L	L	L	L	H	H	L	L
H	X	L	L	X	L	Z	H
X	H	L	L	X	H	Z	L
L	L	H	X	L	X	H	Z
L	L	X	H	H	X	L	Z
H	H	H	H	X	X	Z	Z
L	L	L	L	L	L	H	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V ($\overline{OE}_n$)
I_{IL}	Input LOW Current			−120	µA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{OZH}	Output Leakage Current		0	20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current		0	−20	µA	Max	V_{OUT} = 0.5V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		14	20	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		75	92	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		38	50	mA	Max	V_O = HIGH Z
C_{IN}	Input Capacitance		8		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.8	4.3	1.0	4.3	ns
t_{PHL}	In to $\overline{On}$	1.0	2.0	4.3	1.0	4.3	
t_{PZH}	Output Enable Time	3.4	5.6	11.6	3.4	11.6	ns
t_{PZL}		3.4	7.8	11.6	3.4	11.6	
t_{PHZ}	Output Disable Time	1.8	4.0	6.6	1.8	6.6	ns
t_{PLZ}		1.8	4.4	6.6	1.8	6.6	

Extended AC Characteristics

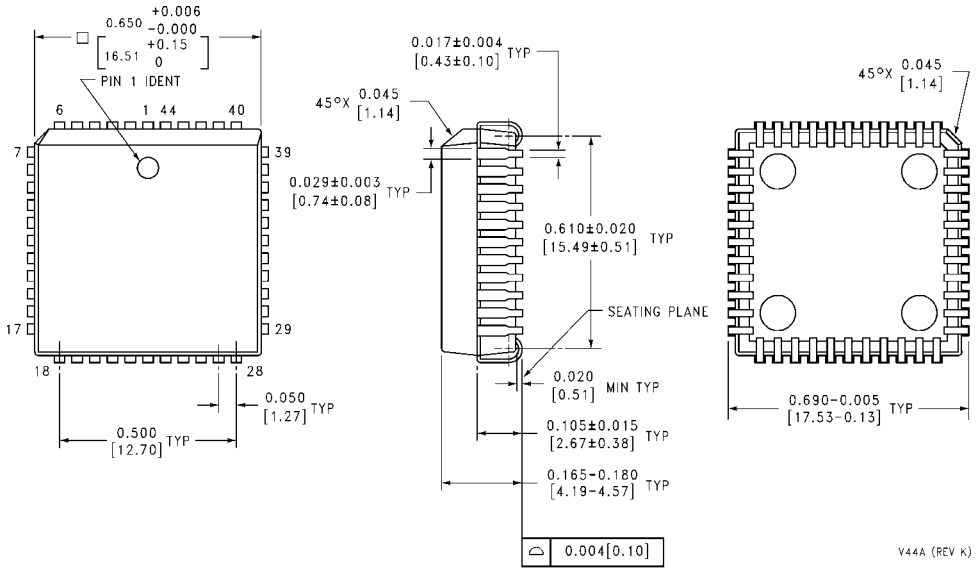
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, 16 Outputs Switching (Note 4)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 5)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	6.0	3.2	8.2	ns
t_{PHL}	In to $\overline{On}$	1.0	6.0	3.2	8.2	
t_{PZH}	Output Enable Time	3.4	14.5			ns
t_{PZL}		3.4	14.5			
t_{PHZ}	Output Disable Time	1.8	6.6			ns
t_{PLZ}		1.8	6.6			
t_{OSHL} (Note 3)	Pin-to-Pin Skew for HL Transitions		1.4			ns
t_{OSLH} (Note 3)	Pin-to-Pin Skew for LH Transitions		1.6			ns
t_{OST} (Note 3)	Pin-to-Pin Skew for HL/LH Transitions		3.0			ns

Note 3: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase. This specification is guaranteed but not tested.

Note 4: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

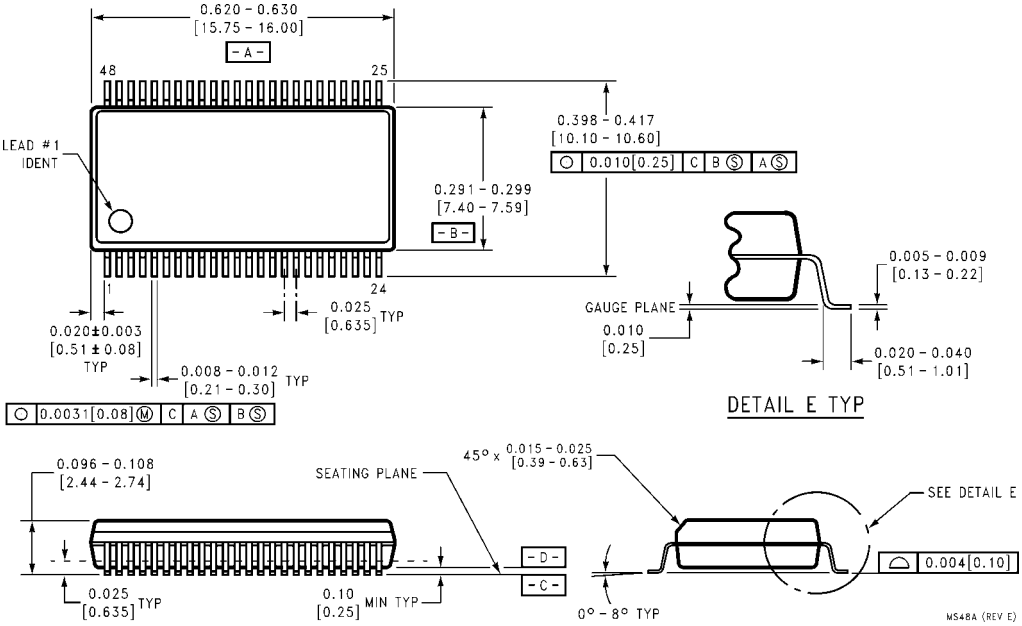
Note 5: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Physical Dimensions inches (millimeters) unless otherwise noted



44-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.650 Square
Package Number V44A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS48A

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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October 1989
Revised August 1999

74FR16541
16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The 74FR16541 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

Features

- Non-inverting buffers
- 3-STATE outputs drive bus lines
- Output sink capability of 64 mA, source capability of 15 mA
- Separate 3-STATE control pins for each byte
- Guaranteed multiple output switching, 250 pF delays and pin-to-pin skew
- 16-bit version of the 74F541, 74F244 or 74FR244

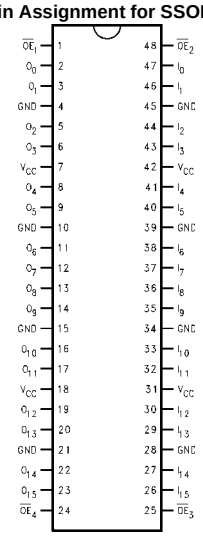
Ordering Code:

Order Number	Package Number	Package Description
74FR16541QC	V44A	44-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.650 Square
74FR16541SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide

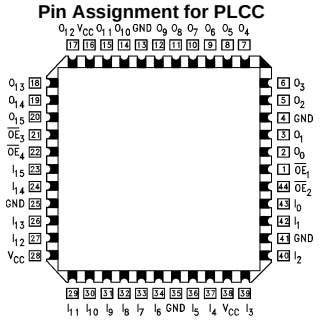
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

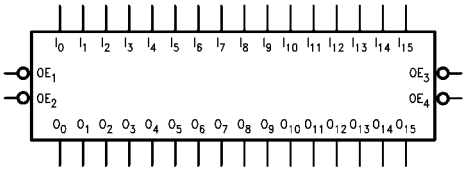
Pin Assignment for SSOP



Pin Assignment for PLCC



Logic Symbol



Pin Descriptions

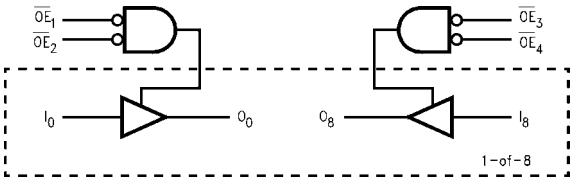
Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs
I_0–I_{15}	Inputs
O_0–O_{15}	3-STATE Outputs

Truth Table

Inputs						Outputs	
Byte1 [0:7]		Byte2 [8:15]		I_0–I_7	I_8–I_{15}	O_0–O_7	O_8–O_{15}
$\overline{OE}_1$	$\overline{OE}_2$	$\overline{OE}_3$	$\overline{OE}_4$				
L	L	L	L	H	H	H	H
H	X	L	L	X	L	Z	L
X	H	L	L	X	H	Z	H
L	L	H	X	L	X	L	Z
L	L	X	H	H	X	H	Z
H	H	H	H	X	X	Z	Z
L	L	L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4 2.0			V	Min	I_{OH} = −3 mA I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V ($\overline{OE_n}$)
I_{IL}	Input LOW Current			−120	µA	Max	V_{IN} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{OZH}	Output Leakage Current		0	20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current		0	−20	µA	Max	V_{OUT} = 0.5V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		35	50	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current		92	110	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current		36	50	mA	Max	V_O = HIGH Z
C_{IN}	Input Capacitance		8		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	2.8	4.3	1.5	4.3	ns
t_{PHL}	I_n to O_n	1.5	2.4	4.3	1.5	4.3	
t_{PZH}	Output Enable Time	3.6	5.8	11.6	3.6	11.6	ns
t_{PZL}		3.6	6.6	11.6	3.6	11.6	
t_{PHZ}	Output Disable Time	1.8	4.0	6.6	1.8	6.6	ns
t_{PLZ}		1.8	4.1	6.6	1.8	6.6	

Extended AC Characteristics

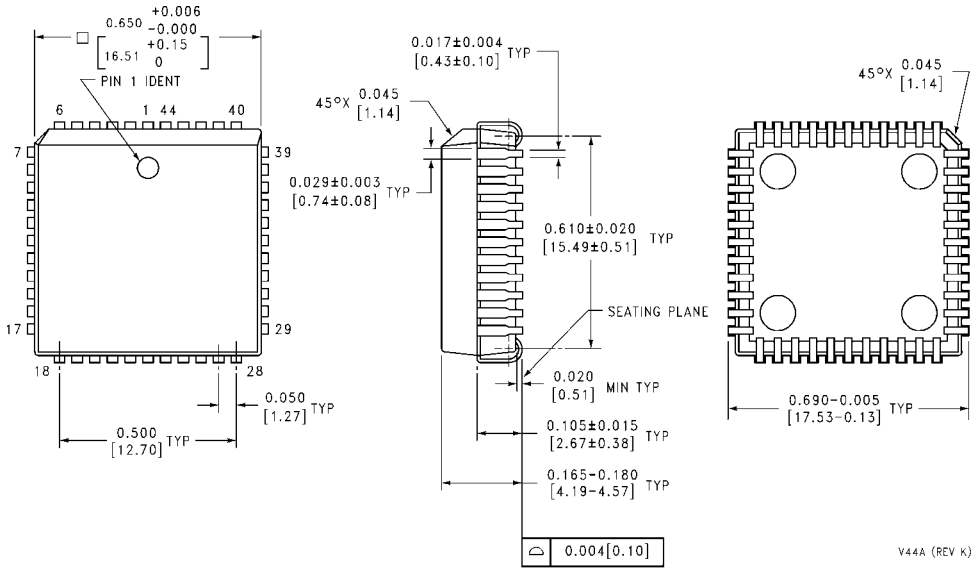
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, 16 Outputs Switching (Note 4)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 5)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	5.7	3.0	9.0	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.5	5.7	3.0	9.0	
t_{PZH}	Output Enable Time	3.6	12.5			ns
t_{PZL}		3.6	12.5			
t_{PHZ}	Output Disable Time	1.8	6.6			ns
t_{PLZ}		1.8	6.6			
t_{osHL} (Note 3)	Pin-to-Pin Skew for HL Transitions		1.5			ns
t_{osLH} (Note 3)	Pin-to-Pin Skew for LH Transitions		1.3			ns
t_{ost} (Note 3)	Pin-to-Pin Skew for HL/LH Transitions		2.0			ns

Note 3: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{osHL}), LOW-to-HIGH, (t_{osLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{ost}). Specifications guaranteed with all outputs switching in phase.

Note 4: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

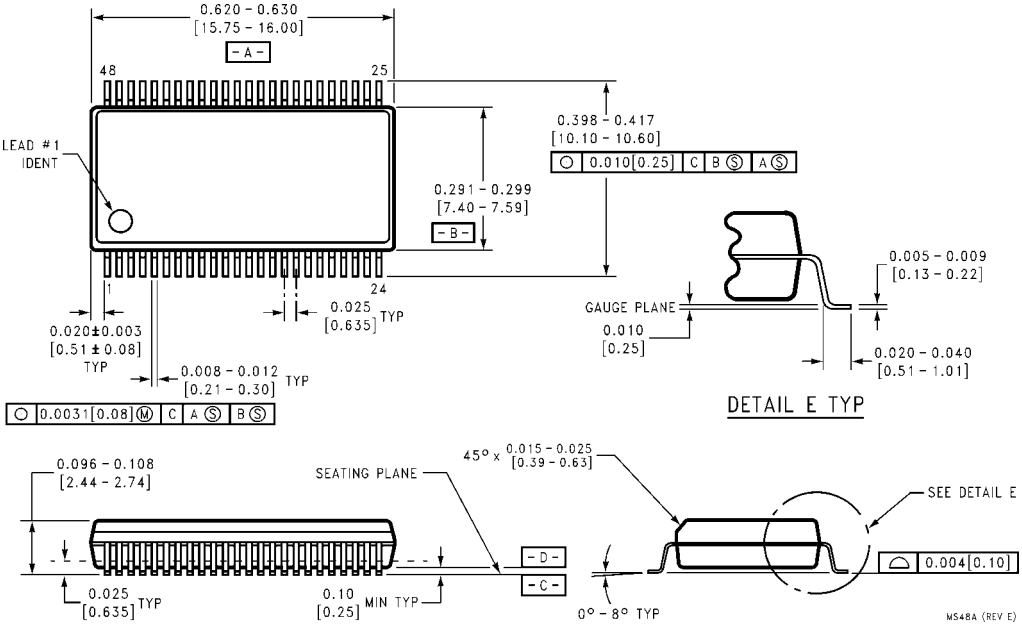
Note 5: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Physical Dimensions inches (millimeters) unless otherwise noted



44-Lead Plastic Lead Chip Carrier (PLCC), JEDEC MO-047, 0.650 Square
Package Number V44A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS48A

FAIRCHILD SEMICONDUCTOR™

January 1991
Revised August 1999

74FR2240
Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The 74FR2240 is an inverting octal buffer and line driver designed to drive capacitive inputs of MOS memory devices, address and clock lines or act as a low undershoot general purpose bus driver.

Features

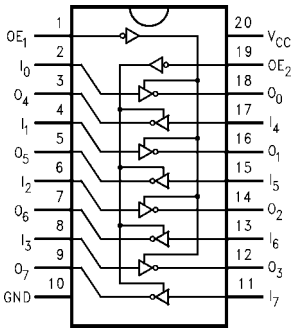
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 12 mA and source 15 mA
- 25Ω series resistors in outputs eliminate the need for external resistors
- Designed to drive the capacitive inputs of MOS devices

Ordering Code:

Order Number	Package Number	Package Description
74FR2240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR2240PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active-LOW)
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.5	V	Min	I_{OL} = 1 mA
				0.75	V	Min	I_{OL} = 12 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		9	13	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		37	45	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		30	38	mA	Max	Outputs 3-STATE

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.7	3.3	4.7	1.7	4.7	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.7	2.9	4.7	1.7	4.7	
t_{PZH}	Output Enable Time	2.6	4.0	8.5	2.6	8.5	ns
t_{PZL}		2.6	6.3	8.5	2.6	8.5	
t_{PHZ}	Output Disable Time	2.1	3.9	6.6	2.1	6.6	ns
t_{PLZ}		2.1	3.4	6.6	2.1	6.6	

Extended AC Electrical Characteristics

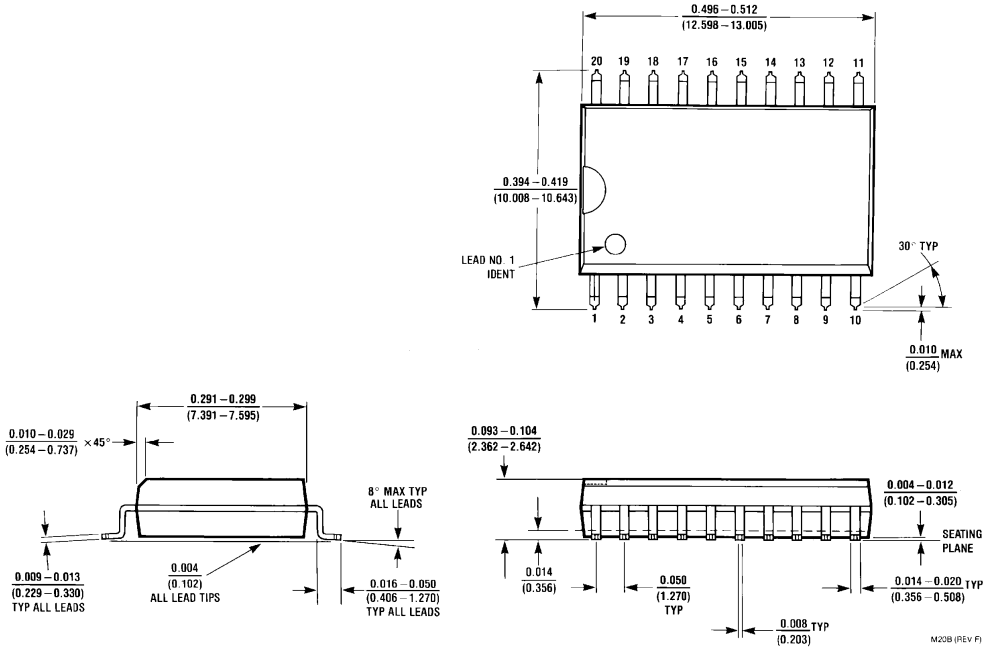
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.7	6.4	4.2	8.6	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.7	6.4	4.2	8.6	
t_{PZH}	Output Enable Time	2.6	8.9			ns
t_{PZL}		2.6	8.9			
t_{PHZ}	Output Disable Time	2.1	6.8			ns
t_{PLZ}		2.1	6.8			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		1.0			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.1			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.0			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

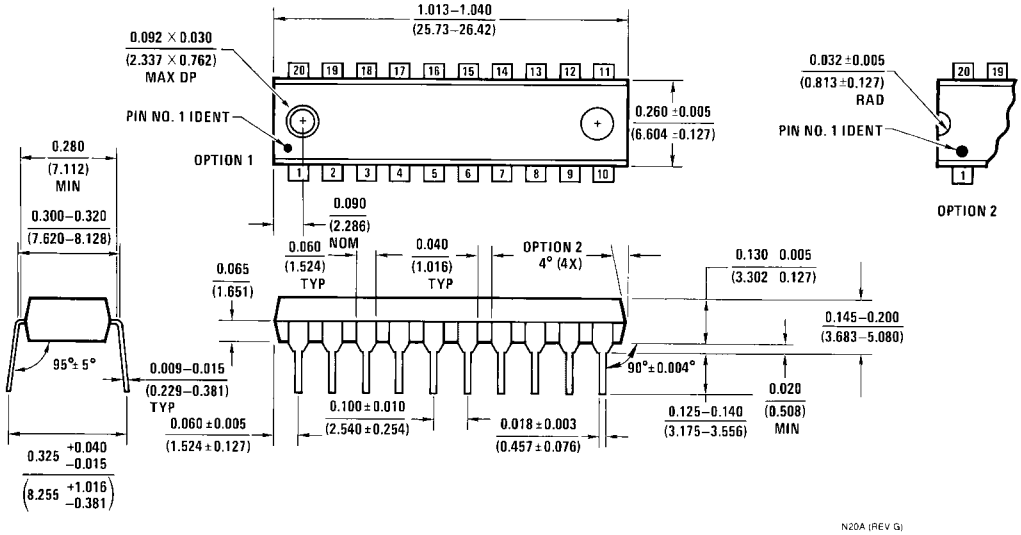
Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

June 1991
Revised August 1999

74FR2244
Octal Buffer/Line Driver with 25Ω Series Resistors in the Outputs

General Description

The 74FR2244 is a non-inverting octal buffer and line driver designed to drive capacitive inputs of MOS memory devices, address and clock lines or act as a low undershoot general purpose bus driver.

Features

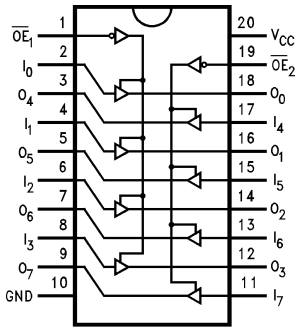
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 12 mA and source 15 mA
- 25Ω series resistors in outputs eliminate the need for external resistors
- Designed to drive the capacitive inputs of MOS devices

Ordering Code:

Order Number	Package Number	Package Description
74FR2244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74FR2244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active-LOW)
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.5	V	Min	I_{OL} = 1 mA
				0.75	V	Min	I_{OL} = 12 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			40	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current			70	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current			46	mA	Max	Outputs 3-STATE

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.6	4.4	1.0	4.4	ns
t_{PHL}		1.0	1.8	4.4	1.0	4.4	
t_{PZH}	Output Enable Time	2.5	4.8	7.1	2.5	7.1	ns
t_{PZL}		2.5	3.9	7.1	2.5	7.1	
t_{PHZ}	Output Disable Time	1.6	3.7	6.4	1.6	6.4	ns
t_{PLZ}		1.6	3.6	6.4	1.6	6.4	

Extended AC Electrical Characteristics

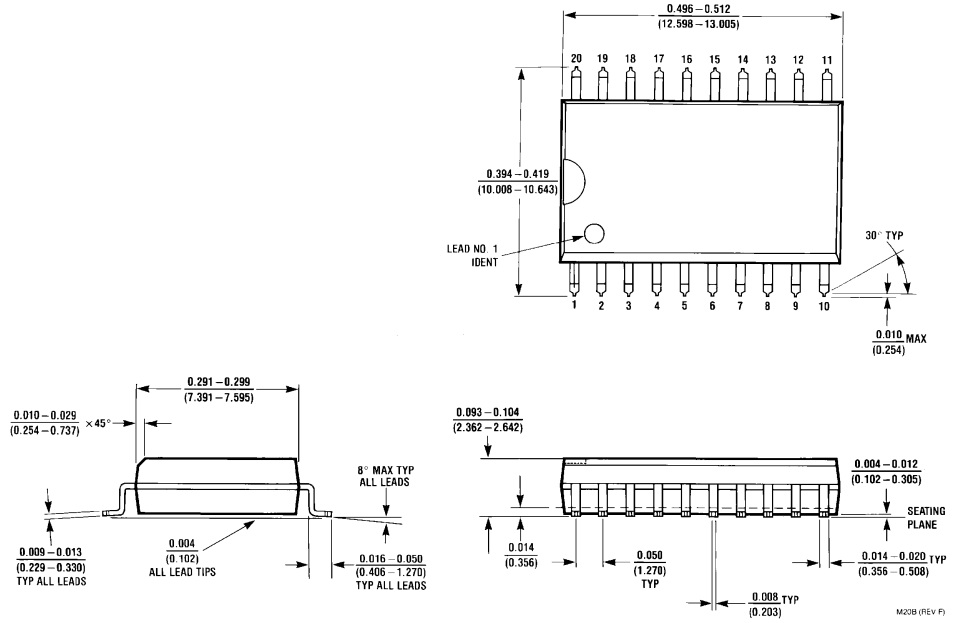
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	5.9	2.7	9.7	ns
t_{PHL}		1.0	5.9	2.7	9.7	
t_{PZH}	Output Enable Time	2.5	8.0			ns
t_{PZL}		2.5	8.0			
t_{PHZ}	Output Disable Time	1.6	7.0			ns
t_{PLZ}		1.6	7.0			
t_{OSHL}	Pin-to-Pin Skew for HL Transitions (Note 5)		1.5			ns
t_{OSLH}	Pin-to-Pin Skew for LH Transitions (Note 5)		1.5			ns
t_{OST}	Pin-to-Pin Skew for HL/LH Transitions (Note 5)		3.0			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

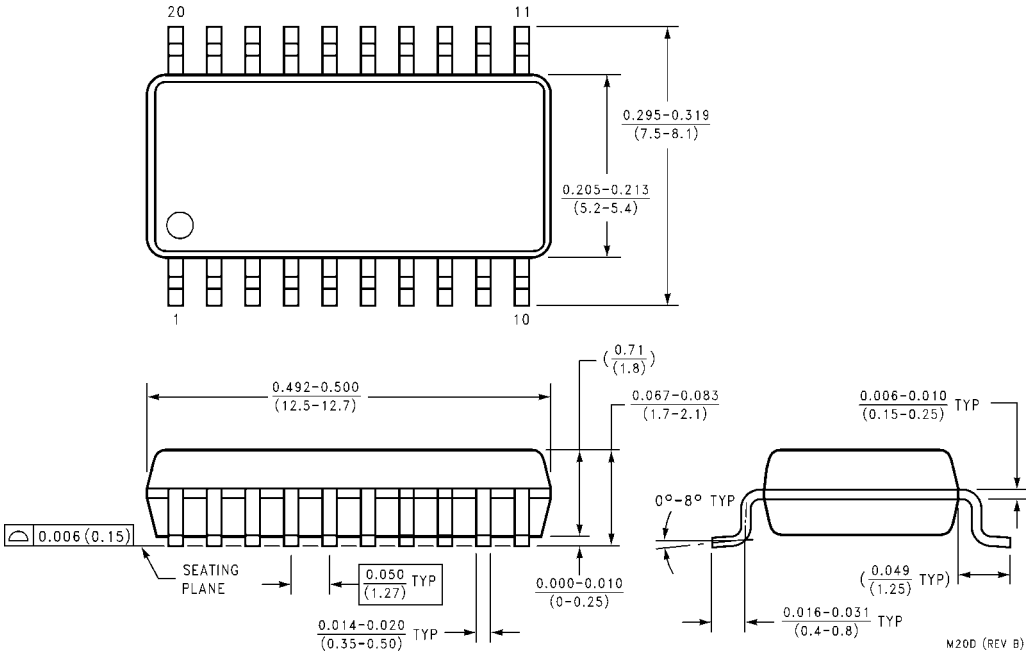
Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted

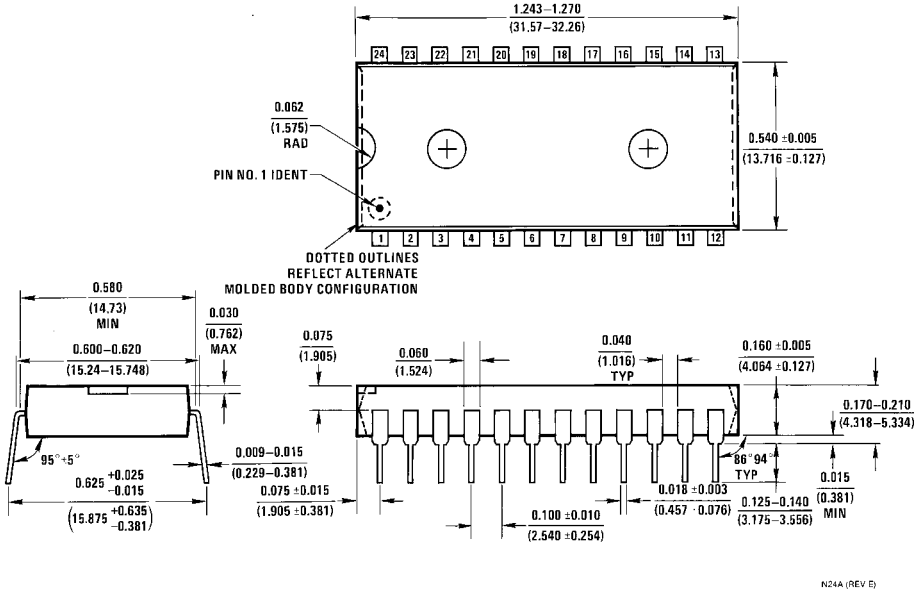


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

April 1995
Revised August 1999

74FR2245
Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The 74FR2245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 64 mA on the A Port. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a High Z condition.

Features

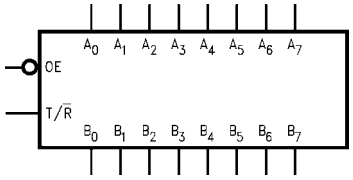
- Non-inverting buffers
- Bidirectional data path
- Guaranteed pin-to-pin skew
- 25Ω series resistors in B outputs eliminate the need for external resistors
- 3-STATE outputs drive bus lines or buffer memory address resistors

Ordering Code:

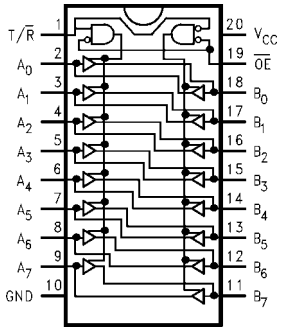
Order Number	Package Number	Package Description
74FR2245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" letter to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

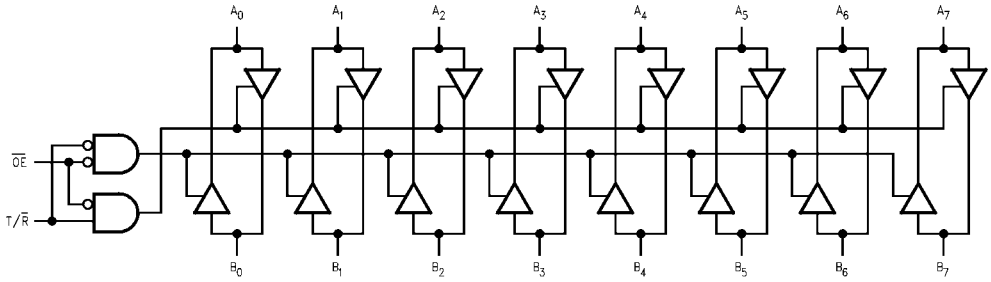
Pin Names	Description
$\overline{OE}$	Output Enable Input (Active-LOW)
$T/\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Output
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage			0.5	V	Max	I_{OL} = 1 mA (B_n)
				0.75	V	Max	I_{OL} = 12 mA (B_n)
				0.55	V	Max	I_{OL} = 64 mA (A_n)
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V ($\overline{OE}$, T/$\overline{R}$)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, T/$\overline{R}$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−250	µA	Max	V_{IN} = 0.5V ($\overline{OE}$, T/$\overline{R}$)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
$I_{IH} + I_{OZH}$	Output Leakage Current			25	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−150	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n)
I_{CCH}	Power Supply Current		55	75	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		75	110	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		55	75	mA	Max	Outputs 3-STATE
C_{IN}	Input Capacitance		8.0		pF	5.0	$\overline{OE}$, T/$\overline{R}$
			17.0		pF	5.0	A_n, B_n

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0		4.4	1.0	4.4	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0		4.4	1.0	4.4	
t_{PZH}	Output Enable Time	2.5		7.5	2.5	7.5	ns
t_{PZL}		2.5		7.5	2.5	7.5	
t_{PHZ}	Output Disable Time	1.7		6.5	1.7	6.5	ns
t_{PLZ}		1.7		6.5	1.7	6.5	

Extended AC Electrical Characteristics

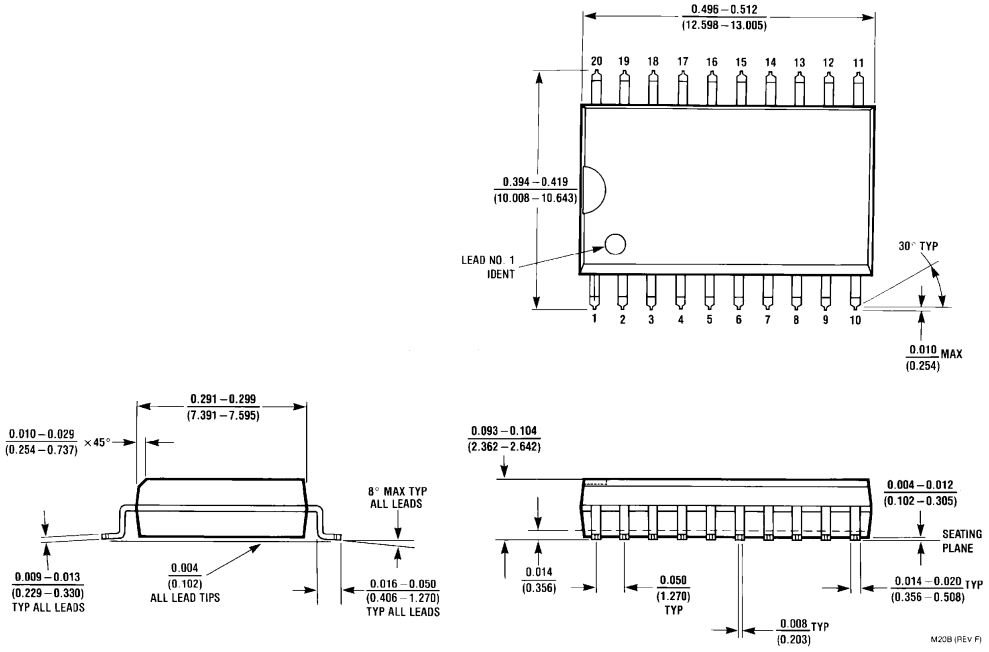
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	7.0	2.5	10.0	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	7.0	2.5	10.0	
t_{PZH}	Output Enable Time	2.5	10.0			ns
t_{PZL}		2.5	10.0			
t_{PHZ}	Output Disable Time	1.3	6.5			ns
t_{PLZ}		1.3	6.5			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		1.7			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.0			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.3			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1991
Revised August 1999

74FR240
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The 74FR240 is an inverting octal buffer and line driver designed to be employed as memory and address driver, clock driver and bus oriented transmitter or receiver.

Features

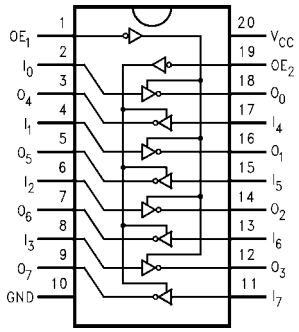
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 64 mA and source 15 mA
- Guaranteed pin-to-pin skew

Ordering Code:

Order Number	Package Number	Package Description
74FR240SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74FR240PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active-LOW)
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input Low Current			−150	µA	Max	V_{IN} = 0.5V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		9	13	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		37	45	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		31	38	mA	Max	Outputs 3-STATE
C_{IN}	Input Capacitance		8.0		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	3.3	4.7	1.0	4.7	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	2.9	4.7	1.0	4.7	
t_{PZH}	Output Enable Time	2.6	4.0	7.0	2.6	7.0	ns
t_{PZL}		2.6	6.3	7.0	2.6	7.0	
t_{PHZ}	Output Disable Time	1.7	3.3	6.6	1.7	6.6	ns
t_{PLZ}		1.7	2.9	6.6	1.7	6.6	

Extended AC Electrical Characteristics

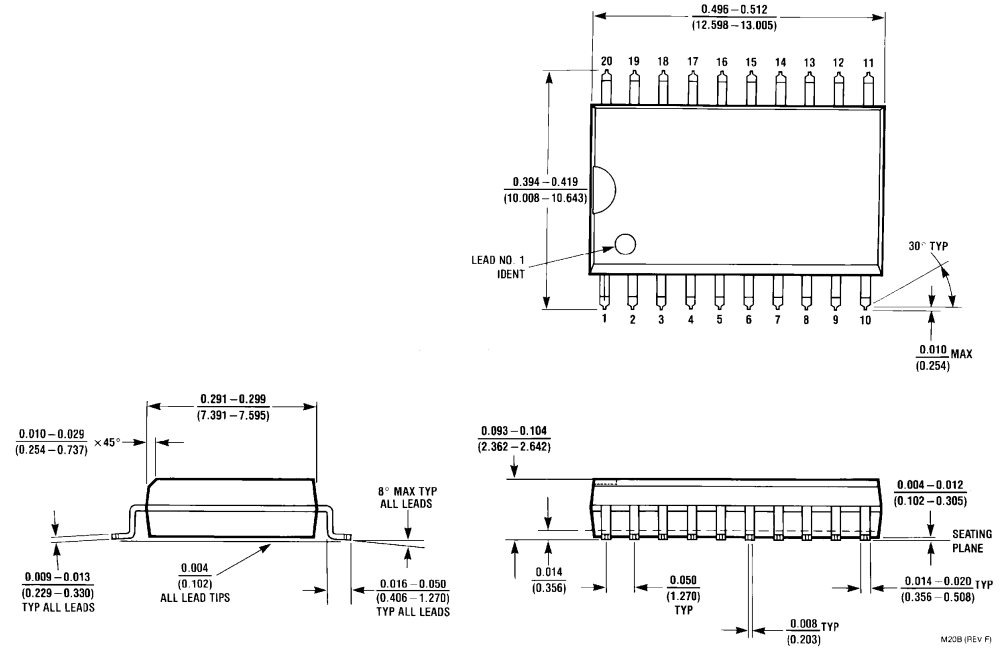
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	6.4	2.3	8.3	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	6.4	2.3	8.3	
t_{PZH}	Output Enable Time	2.6	7.2			ns
t_{PZL}		2.6	7.2			
t_{PHZ}	Output Disable Time	1.7	6.8			ns
t_{PLZ}		1.7	6.8			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		2.0			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.1			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.1			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

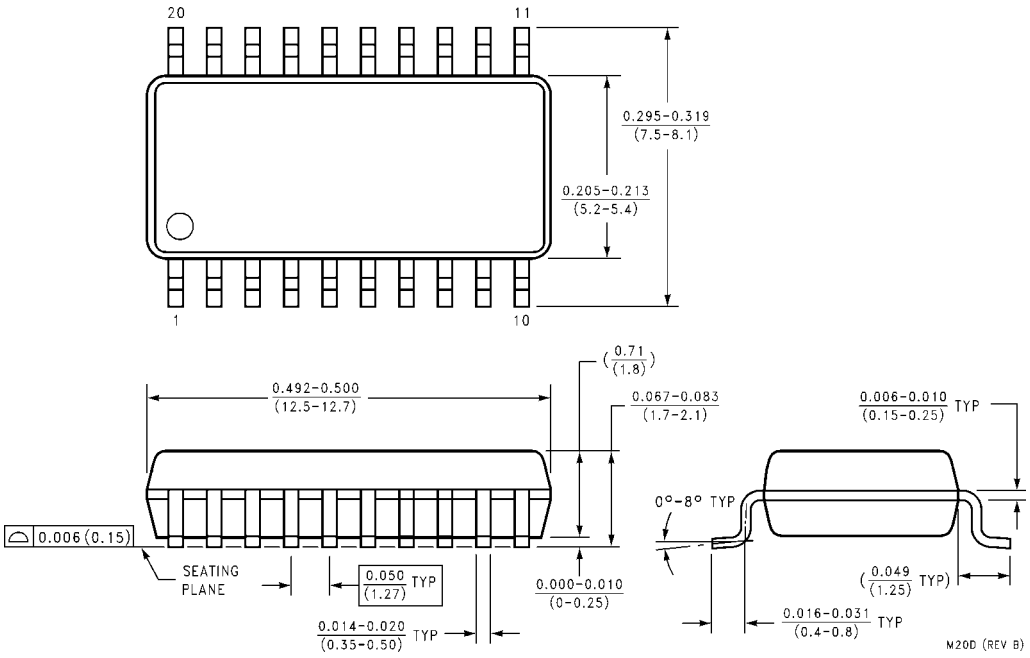
Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted

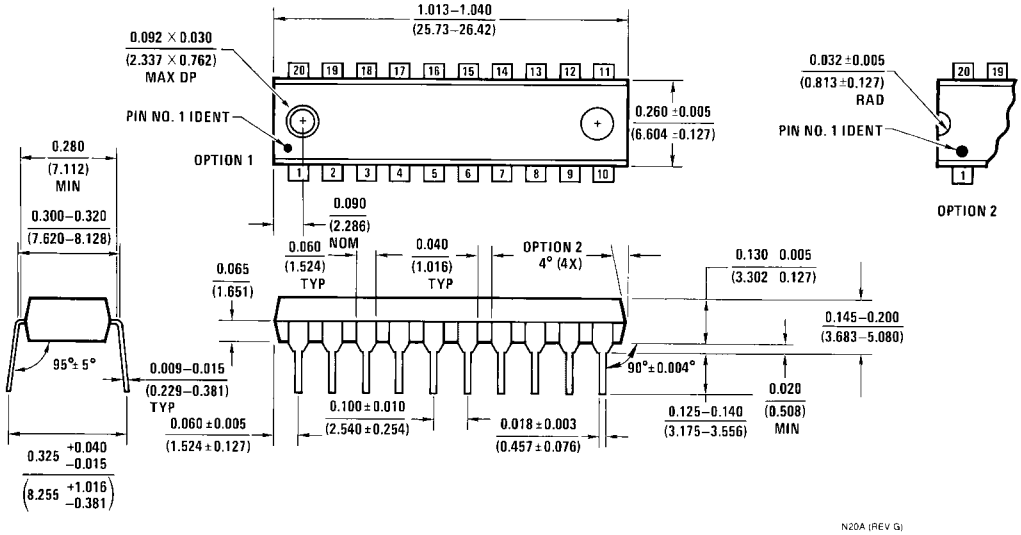


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

December 1990
Revised August 1999

74FR244
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The 74FR244 is a non-inverting octal buffer and line driver designed to be employed as memory and address driver, clock driver and bus-oriented transmitter/receiver.

Features

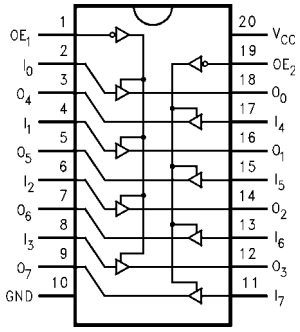
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 64 mA and source 15 mA
- Guaranteed pin-to-pin skew

Ordering Code:

Order Number	Package Number	Package Description
74FR244SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74FR244PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$,–$\overline{OE}_2$	Output Enable Input (Active-LOW)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	–65°C to +150°C
Ambient Temperature Under Bias	–55°C to +125°C
Junction Temperature Under Bias	–55°C to +150°C
V_{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
Input Voltage (Note 2)	–0.5V to +7.0V
Input Current (Note 2)	–30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	–0.5V to V_{CC}
3-STATE Output	–0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			–1.2	V	Min	I_{IN} = –18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = –3 mA
		2.0			V	Min	I_{OH} = –15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			–150	µA	Max	V_{IN} = 0.5V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			–20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	–100		–225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		30	50	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		55	75	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		35	50	mA	Max	Outputs 3-STATED
C_{IN}	Input Capacitance		8.0		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.6	3.9	1.0	3.9	ns
t_{PHL}		1.0	1.8	3.9	1.0	3.9	
t_{PZH}	Output Enable Time	2.5	4.8	6.6	2.5	6.6	ns
t_{PZL}		2.5	3.9	6.6	2.5	6.6	
t_{PHZ}	Output Disable Time	1.6	3.7	6.4	1.6	6.4	ns
t_{PLZ}		1.6	3.6	6.4	1.6	6.4	

Extended AC Characteristics

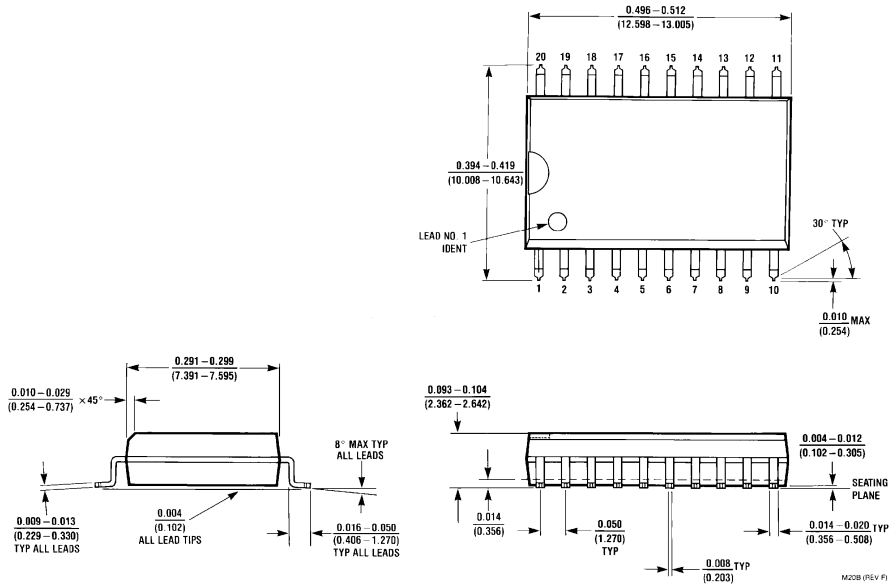
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	5.0	2.3	7.3	ns
t_{PHL}		1.0	5.0	2.3	7.3	
t_{PZH}	Output Enable Time	2.5	7.7			ns
t_{PZL}		2.5	7.7			
t_{PHZ}	Output Disable Time	1.6	6.5			ns
t_{PLZ}		1.6	6.5			
t_{OSHL}	Pin-to-Pin Skew for HL Transitions (Note 5)		1.6			ns
t_{OSLH}	Pin-to-Pin Skew for LH Transitions (Note 5)		1.0			ns
t_{OST}	Pin-to-Pin Skew for HL/LH Transitions (Note 5)		3.5			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

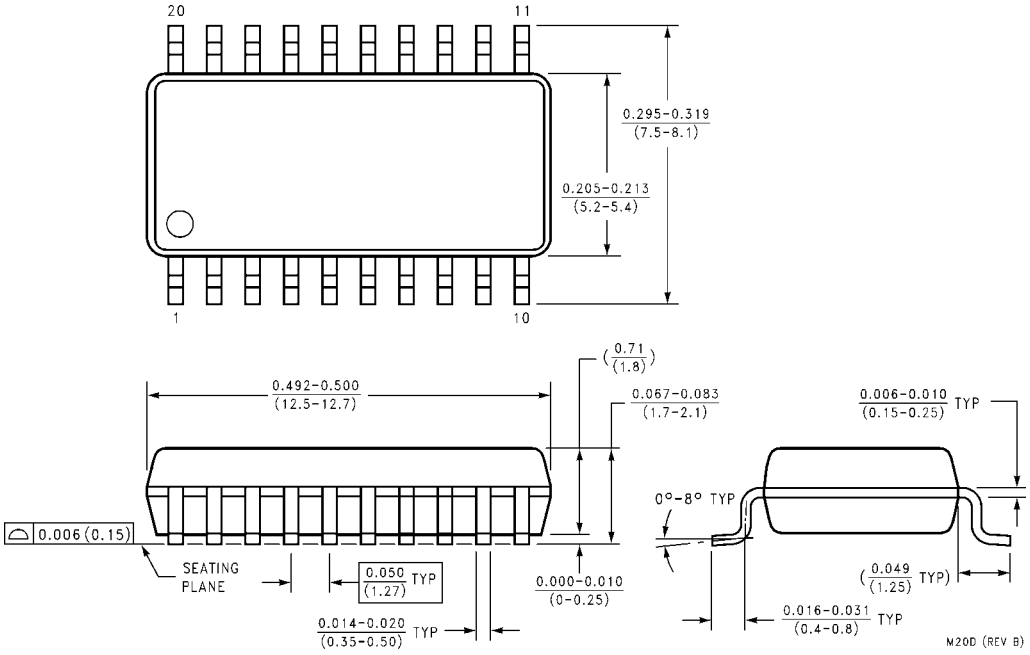
Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specification guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted

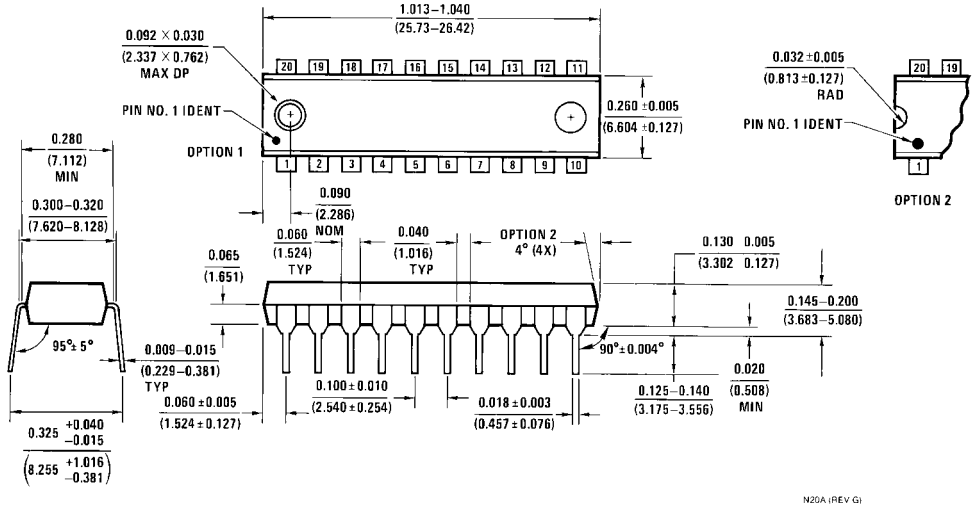


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

August 1990
Revised August 1999

74FR245
Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The 74FR245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 64 mA on both the A and B Ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a High Z condition.

Features

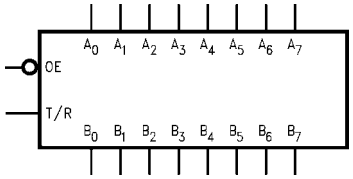
- Non-inverting buffers
- Bidirectional data path
- A and B output sink capability of 64 mA, source capability of 15 mA
- Guaranteed pin-to-pin skew

Ordering Code:

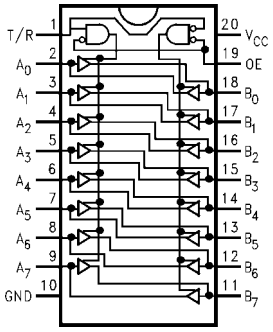
Order Number	Package Number	Package Description
74FR245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74FR245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

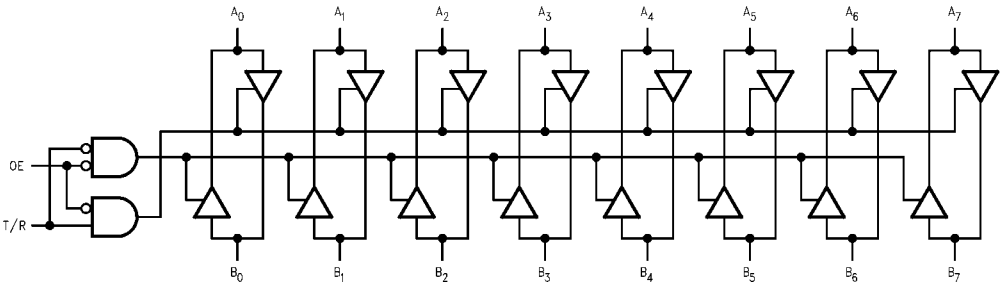
Pin Names	Description
$\overline{OE}$	Output Enable Input (Active-LOW)
$T/\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Output
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V ($\overline{OE}$, T/$\overline{R}$)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, T/$\overline{R}$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−250	µA	Max	V_{IN} = 0.5V ($\overline{OE}$, T/$\overline{R}$)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
$I_{IH} + I_{OZH}$	Output Leakage Current			25	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−150	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n)
I_{CCH}	Power Supply Current		55	75	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		75	110	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		55	75	mA	Max	Outputs 3-STATE
C_{IN}	Input Capacitance		8.0		pF	5.0	$\overline{OE}$, T/$\overline{R}$
			17.0		pF	5.0	A_n, B_n

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.6	3.9	1.0	3.9	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	1.7	3.9	1.0	3.9	
t_{PZH}	Output Enable Time	2.5	5.0	7.0	2.5	7.0	ns
t_{PZL}		2.5	4.3	7.0	2.5	7.0	
t_{PHZ}	Output Disable Time	1.7	3.7	6.5	1.7	6.5	ns
t_{PLZ}		1.7	3.6	6.5	1.7	6.5	

Extended AC Characteristics

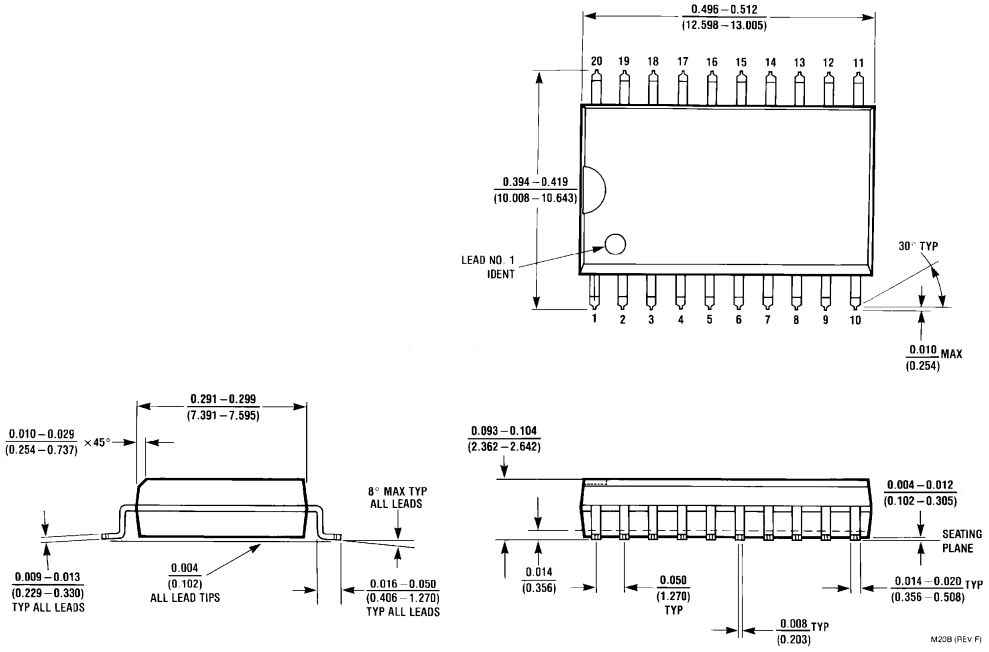
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	5.9	2.5	7.5	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	5.9	2.5	7.5	
t_{PZH}	Output Enable Time	2.5	11.9			ns
t_{PZL}		2.5	11.9			
t_{PHZ}	Output Disable Time	1.3	6.5			ns
t_{PLZ}		1.3	6.5			
t_{OSHL} (Note 5)	Pin to Pin Skew for HL Transitions		1.7			ns
t_{OSLH} (Note 5)	Pin to Pin Skew for LH Transitions		1.0			ns
t_{OST} (Note 5)	Pin to Pin Skew for HL/LH Transitions		3.3			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

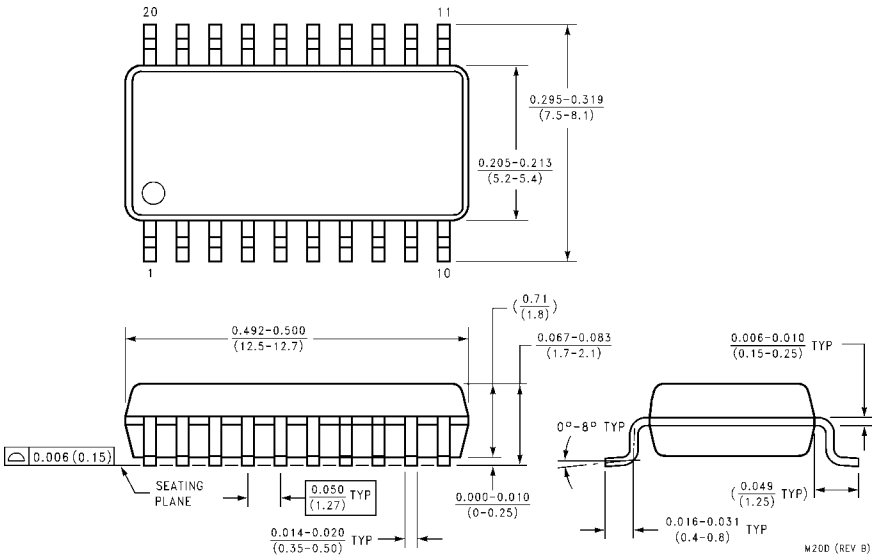
Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted

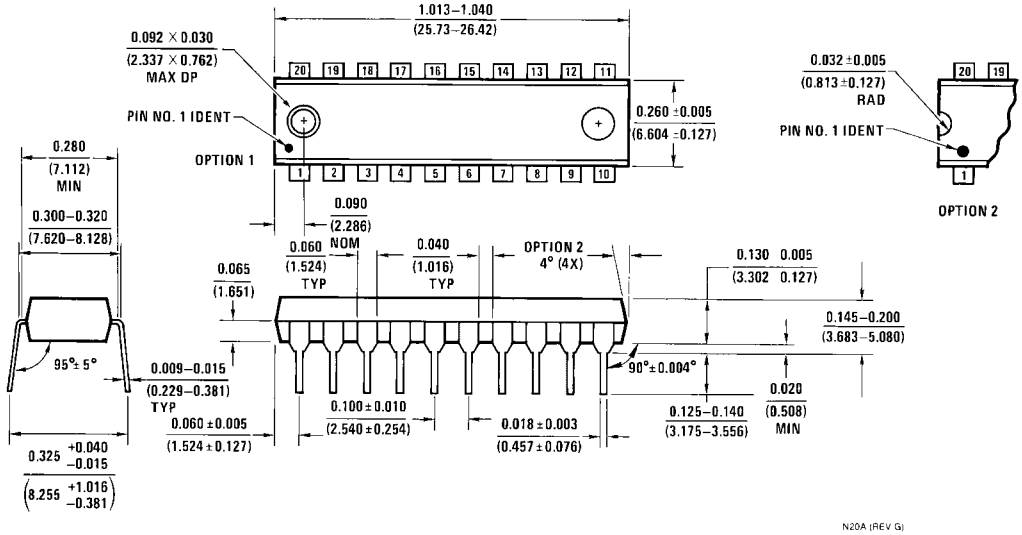


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

July 1992
Revised August 1999

74FR25900
9-Bit, 3-Port Latchable Datapath Multiplexer with 25Ω Output Series Resistors

General Description

The 74FR25900 is a data bus multiplexer routing any of three 9-bit ports to any other one of the three ports. Readback of data latched from any port onto itself is also possible. The 74FR25900 maintains separate control of all latch-enable, output enable and select inputs for maximum flexibility. PINV allows inversion of the data from the C_8 to A_8 or B_8 path. This is useful for control of the parity bit in systems diagnostics.

This device includes 25Ω resistors in series with A and B Port outputs. Resistors minimize undershoot and ringing which may damage or corrupt sensitive device inputs driven by these ports.

Features

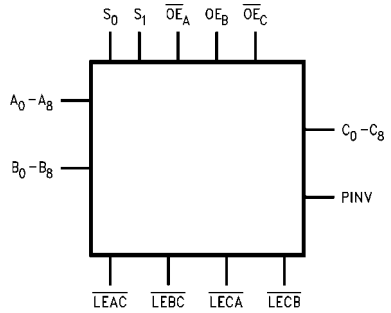
- 25Ω series resistors in the port A and B outputs eliminate the need for external resistors when driving MOS inputs such as DRAM arrays
- 9-bit data ports for systems carrying parity bits
- Readback capability for system self checks.
- Independent control lines for maximum flexibility
- Guaranteed multiple output switching and 250 pF load delays
- Outputs optimized for dynamic bus drive capability
- PINV parity control facilitates system diagnostics
- 74FR900 option available without output series resistors

Ordering Code:

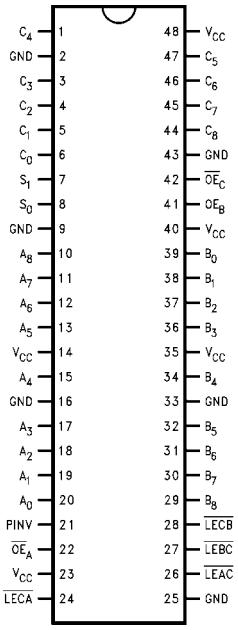
Order Number	Package Number	Package Description
74FR25900SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
$\overline{LExx}$	Latch Enable Inputs
$\overline{OE}_x$	Output Enable Inputs
PINV	Parity Invert Input
S_0, S_1	Select Inputs
A_0–A_8	Port A Inputs or 3-STATE Outputs
B_0–B_8	Port B Inputs or 3-STATE Outputs
C_0–C_8	Port C Inputs or 3-STATE Outputs

Functional Description

The 74FR25900 allows 9-bit data to be transferred from any of three 9-bit I/O ports to either of the two remaining I/O ports. The device employs latches in all paths for either transparent or synchronous operation. Readback capability from any port to itself is also possible.

Data transfer within the 74FR25900 is controlled through use of the select (S_0 and S_1) and output-enable ($\overline{OE}_A$, OE_B and $\overline{OE}_C$) inputs as described in Table 1. Additional control is available by use of the latch-enable inputs ($\overline{LEAC}$, $\overline{LECA}$, $\overline{LEBC}$, $\overline{LECB}$) allowing either synchronous or transparent transfers (see Table 2). Table 1 indicates several readback conditions. By latching data on a given port and initiating the readback control configuration, previous data may be read for system verification or diagnostics. This mode may be useful in implementing system diagnostics.

Data at the port to be readback must be latched prior to enabling the outputs on that port. If this is not done, a closed data loop will result causing possible data integrity problems. Note that the A and B Ports allow readback without affecting any other port. C Port, however, requires interruption of either A or B Ports to complete its readback path.

PINV controls inversion of the C_8 bit. A LOW on PINV allows C_8 data to pass unaltered. A HIGH causes inversion of the data. See Table 3. This feature allows forcing of parity errors for use in system diagnostics. This is particularly helpful in 486 processor designs as the 486 does not provide odd/even parity selection internally.

TABLE 1. Datapath Control

Inputs					Function
S_0	S_1	$\overline{OE}_A$	OE_B	$\overline{OE}_C$	
L	X	H	L	L	Port A to Port C
L	L	H	H	H	Port A to Port B
L	O	H	H	L	Port A to B+C
H	L	L	L	H	Port B to Port A
H	X	H	L	L	Port B to Port C
H	O	L	L	L	Port B to A+C
X	H	L	L	H	Port C to Port A
X	H	H	H	H	Port C to Port B
X	H	L	H	H	Port C to A+B
X	X	H	L	H	Outputs Disabled
L	L	L	X	X	(Readback to A) (Note 1)
L	H	L	X	L	(Readback to A or C) (Note 1)
H	L	X	H	X	(Readback to B) (Note 1)
H	H	X	H	L	(Readback to B or C) (Note 1)

Note 1: Readback operation in latched mode only. Transparent operation could result in unpredictable results.

TABLE 2. Latch-Enable Control

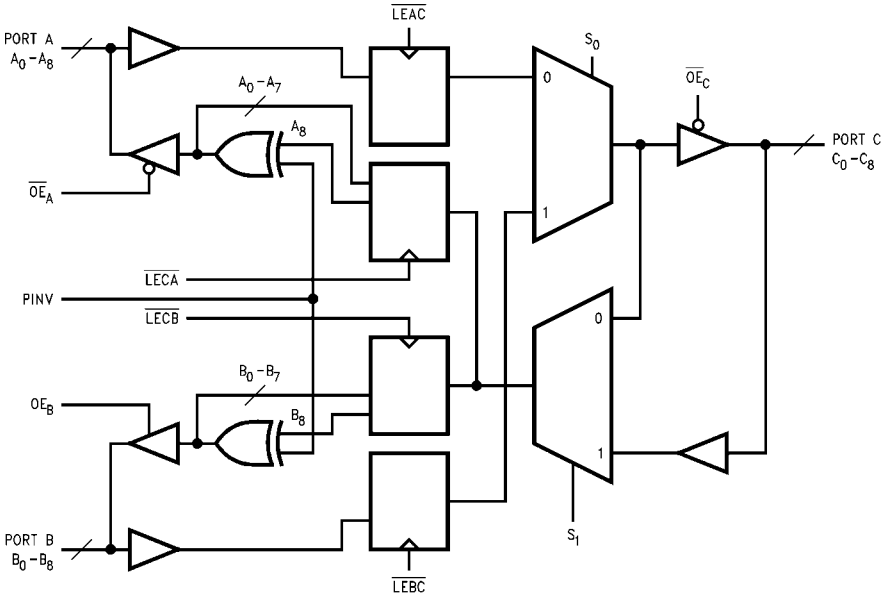
$\overline{LExx}$	Input	Output
L	L	L
L	H	H
H	X	Q_0

TABLE 3. PINV Control

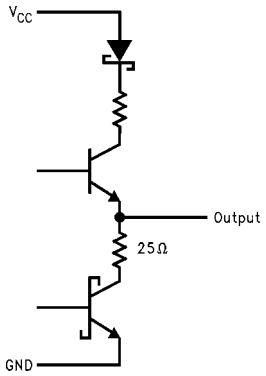
PINV	C_8	A_8 or B_8
L	L	L
L	H	H
H	L	H
H	H	L

Key:
L = LOW Voltage
H = HIGH Voltage Level
Q_0 = Output state prior to $\overline{LExx}$ LOW-to-HIGH transition

Logic Diagram



Schematic of A and B Port Outputs



Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	2000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n, C_n)
		2.0			V	Min	I_{OH} = −15 mA (A_n, B_n, C_n)
V_{OL}	Output LOW Voltage			0.50	V	Min	I_{OL} = 1 mA (A_n, B_n)
				0.75	V	Min	I_{OL} = 12 mA (A_n, B_n)
				0.50	V	Min	I_{OL} = 24 mA (C_n)
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V (Control Inputs)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Control Inputs)
I_{BVIT}	Input High Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n, C_n)
I_{IL}	Input Low Current			−150	µA	Max	V_{IN} = 0.5V (Control Inputs)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Test			3.75	V	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
$I_{IH} + I_{OZH}$	Output Leakage Current			25	µA	Max	V_{OUT} =2.7V (A_n, B_n, C_n)
$I_{IIL} + I_{OZL}$	Output Leakage Current			−150	µA	Max	V_{OUT} = 0.5V (A_n, B_n, C_n)
I_{OS}	Output Short Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V (A_n, B_n, C_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n, C_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n, C_n)
I_{CCH}	Power Supply Current		115	150	mA	Max	All Outputs HIGH (Note 4)
I_{CCL}	Power Supply Current		170	200	mA	Max	All Outputs LOW (Note 4)
I_{CCZ}	Power Supply Current		147	175	mA	Max	Outputs in 3-STATE

Note 4: 2 ports active only

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n or B_n to C_n C_n to A_n or B_n	2.0	4.7	7.5	2.0	7.5	ns
t_{PLH} t_{PHL}	Propagation Delay C_8 to A_8 or B_8 (PINV HIGH)	2.5	4.8	7.5	2.5	7.5	ns
t_{PLH} t_{PHL}	Propagation Delay A_n to B_n, B_n to A_n	4.5	7.0	11.5	4.5	11.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEAC}$ to C_n, $\overline{LEBC}$ to C_n	4.5	6.8	10.0	4.5	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LECA}$ to A_n, $\overline{LECB}$ to B_n	3.5	6.0	10.0	3.5	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay S_0 to C_n	3.0	6.0	10.0	3.0	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay S_1 to A_n or B_n	4.0	7.0	11.5	4.0	11.5	ns
t_{PLH} t_{PHL}	Propagation Delay PINV to A_8 or B_8	2.5	5.5	9.5	2.5	9.5	ns
t_{PZH} t_{PZL}	Output Enable Time C_n	1.5	4.0	6.5	1.5	6.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time C_n	1.5	4.0	6.0	1.5	6.0	ns
t_{PZH} t_{PZL}	Output Enable Time A_n, B_n	1.5	6.0	8.0	1.5	8.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time A_n, B_n	1.5	5.0	7.0	1.5	7.0	ns

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW A_n to $\overline{LEAC}$, B_n to $\overline{LEBC}$	4.5	2.5		4.5		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW A_n to $\overline{LEAC}$, B_n to $\overline{LEBC}$	1.0	–1.5		1.0		ns
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW C_n to $\overline{LECA}$ or $\overline{LECB}$	3.0	1.0		3.0		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW C_n to $\overline{LECA}$ or $\overline{LECB}$	1.0	–1.0		1.0		ns
$t_W(H)$	$\overline{LE}$ Pulse Width LOW	8.0	4.0		8.0		ns

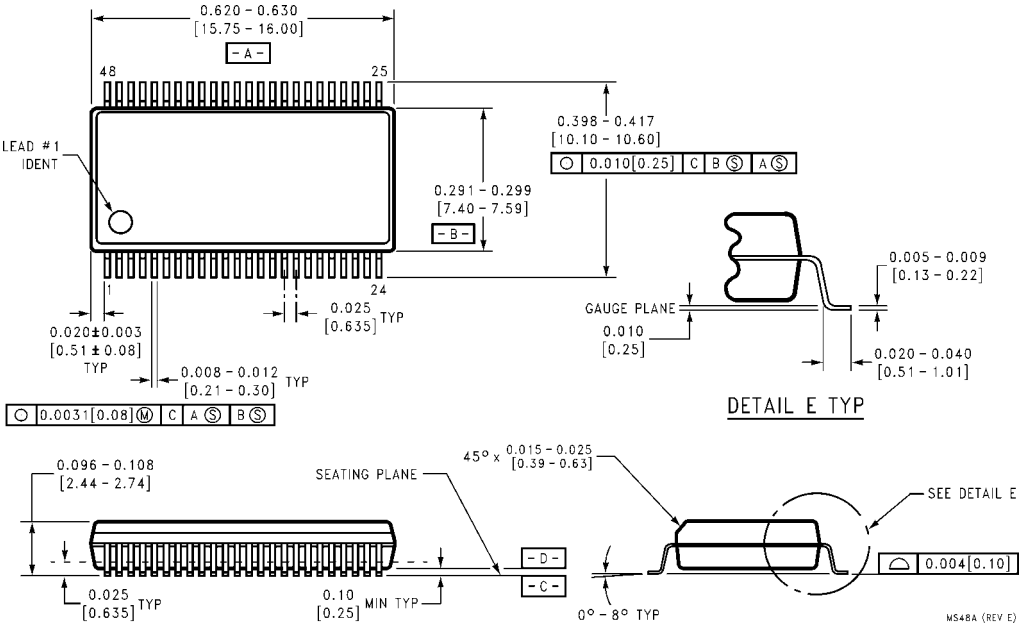
Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Nine Outputs Switching (Note 5)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 6)		Units
		Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n or B_n to C_n C_n to A_n or B_n	2.0	11.5	4.0	12.5	ns
t_{PLH} t_{PHL}	Propagation Delay C_8 to A_8 or B_8 (PINV HIGH)			5.5	13.0	ns
t_{PLH} t_{PHL}	Propagation Delay A_n to B_n, B_n to A_n	4.5	16.0	6.0	16.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEAC}$ to C_n, $\overline{LEBC}$ to C_n	4.5	13.0	5.5	13.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LECA}$ to A_n, $\overline{LECB}$ to B_n	3.5	11.5	5.5	14.5	ns
t_{PLH} t_{PHL}	Propagation Delay S_0 to C_n	3.0	11.0	3.0	14.0	ns
t_{PLH} t_{PHL}	Propagation Delay S_1 to A_n or B_n	4.0	16.5	6.5	16.5	ns
t_{PLH} t_{PHL}	Propagation Delay PINV to A_8 or B_8			4.5	14.5	ns
t_{PZH} t_{PZL}	Output Enable Time C_n	1.5	8.0			ns
t_{PHZ} t_{PLZ}	Output Disable Time C_n	1.5	6.0			ns
t_{PZH} t_{PZL}	Output Enable Time A_n, B_n	1.5	8.0			ns
t_{PHZ} t_{PLZ}	Output Disable Time A_n, B_n	1.5	7.0			ns

Note 5: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 6: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors standard AC load. This specification pertains to single output switching only.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS48A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1991
Revised August 1999

74FR543
Octal Latched Transceiver with 3-STATE Outputs

General Description

The 74FR543 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. Both the A and B outputs will source 15 mA and sink 64 mA.

Features

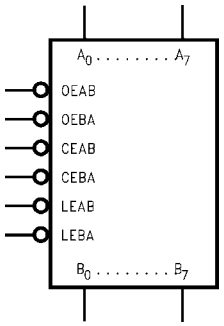
- Functionally equivalent to 74F543
- Back-to-back registers for storage
- Bidirectional data path
- A and B outputs have current sourcing capability of 15 mA and current sinking capability of 64 mA
- Separate controls for data flow in each direction
- Guaranteed pin-to-pin skew
- Guaranteed 4000V minimum ESD protection

Ordering Code:

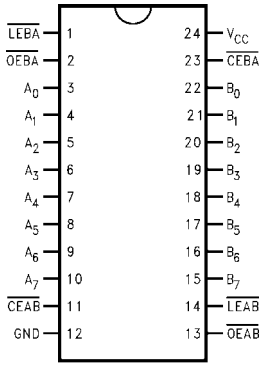
Order Number	Package Number	Package Description
74FR543SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR543SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs
$\overline{LEAB}$, $\overline{LEBA}$	Latch Enable Inputs
$\overline{CEAB}$, $\overline{CEBA}$	Chip Enable Inputs
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Functional Description

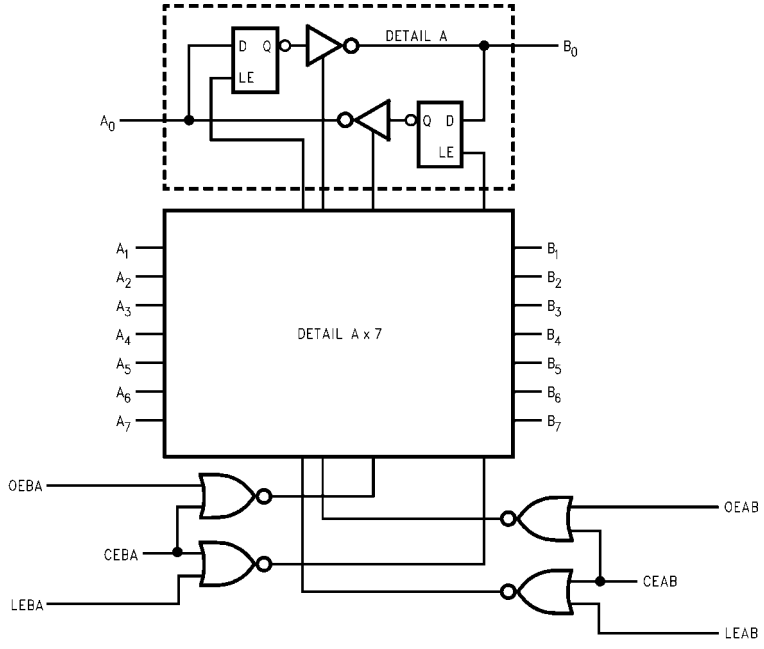
The 74FR543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A-to-B, for example, the A-to-B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from the A Port or take data from the B Port as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a LOW signal on ($\overline{LEAB}$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B-to-A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$.

Data I/O Control Table

Inputs			Latch	Output
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$	Status	Buffers
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		2.0			V	Min	I_{OH} = −15 mA (A_n, (B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Control Pins)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5 (CEAB, CEBA)
				−100	µA	Max	V_{IN} = 0.5 (LEAB, LEBA, OEAB, OEBA)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Test			3.75	µA	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
$I_{IH} + I_{OZH}$	Output Leakage Current			25	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−150	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n)
I_{CCH}	Power Supply Current		59	72	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		87	102	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		69	85	mA	Max	Outputs 3-STATE
C_{IN}	Input Capacitance		8.0		pF	5.0	Control Pins
			17.0		pF	5.0	A_n, B_n

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.3	3.0	4.7	1.3	4.7	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.3	2.6	4.7	1.3	4.7	
t_{PLH}	Propagation Delay	2.3	5.7	8.5	2.3	8.5	ns
t_{PHL}	LEAB to B, LEBA to A	2.3	4.0	8.5	2.3	8.5	
t_{PZH}	Output Enable Time	2.3	4.3	7.4	2.3	7.4	ns
t_{PZL}		2.3	4.9	7.4	2.3	7.4	
t_{PHZ}	Output Disable Time	1.6	3.9	7.0	1.6	7.0	ns
t_{PLZ}		1.6	3.5	7.0	1.6	7.0	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	2.5	0.5		2.5		ns
$t_S(L)$	D_n to LE	2.5	0.1		2.5		
$t_H(H)$	Hold Time, HIGH or LOW	2.0	0.0		2.0		ns
$t_H(L)$	D_n to LE	2.0	–0.6		2.0		
$t_W(H)$	LE Pulse Width HIGH	6.0	3.6		6.0		ns

Extended AC Electrical Characteristics

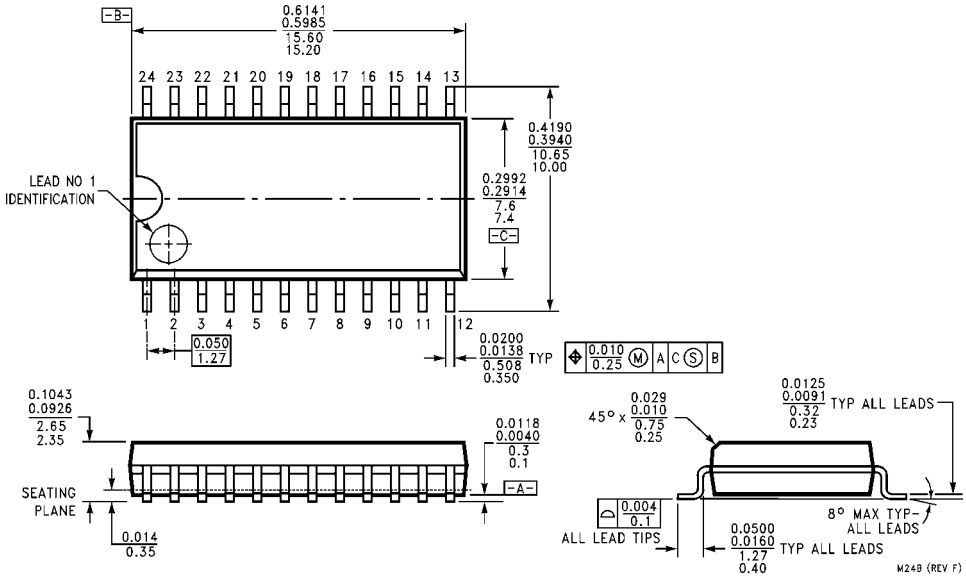
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.3	6.3	3.2	8.7	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.3	6.3	3.2	8.7	
t_{PLH}	Propagation Delay	2.3	10.2	4.2	12.8	ns
t_{PHL}	LEAB to B, LEBA to A	2.3	10.2	4.2	12.8	
t_{PZH}	Output Enable Time	2.3	11.1			ns
t_{PZL}		2.3	11.1			
t_{PHZ}	Output Disable Time	1.6	7.2			ns
t_{PLZ}		1.6	7.2			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		1.2			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.0			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.1			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

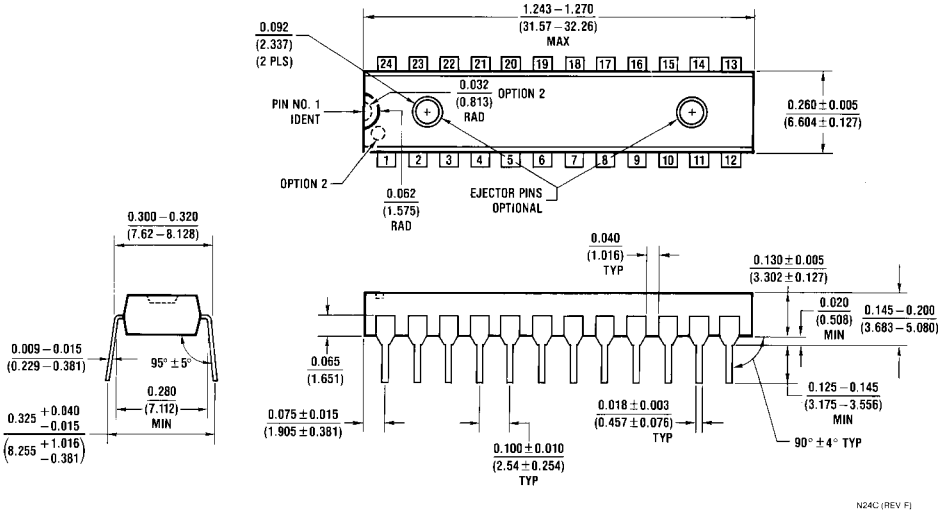
Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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January 1991
Revised August 1999

74FR573
Octal D-Type Latch with 3-STATE Outputs

General Description

The 74FR573 is a high speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

This device is functionally identical to the 74F573.

Features

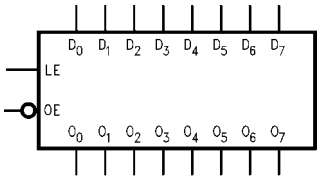
- Broadside pinout aids in PC layout
- Functionally identical to the 74F373, 74F573
- Outputs have current sourcing capability of 15 mA and current sinking capability of 64 mA
- Guaranteed pin-to-pin skew

Ordering Code:

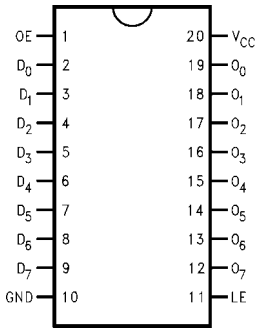
Order Number	Package Number	Package Description
74FR573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR573PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active-LOW)
LE	Latch Enable Input (Active-HIGH)
D_0–D_7	Data Inputs
O_0–O_7	3-STATE Latch Outputs

Functional Description

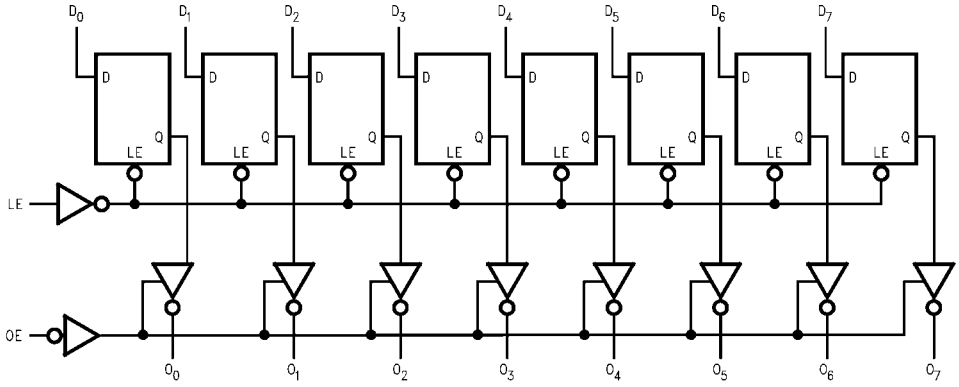
The 74FR573 contains eight D-type latches with 3-STATE output buffers. When the latch enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode, but this does not interfere with entering new data into the latches.

Function Table

Inputs			Output
$\overline{OE}$	LE	D_n	O_n
L	H	H	H
L	H	L	L
L	L	X	O_{n-1}
H	X	X	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to 125°C
Junction Temperature under Bias	−55° to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5 to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to 5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH	2.4			V	Min	I_{OH} = −3 mA
	Voltage	2.0			V	Min	I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{IOL} = 64 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5V Data Inputs
				−100	µA	Max	V_{IN} = 0.5V Control Inputs
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	μA_{IOD} = 150 mV, All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		26	32	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		55	65	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		32	40	mA	Max	Outputs 3-STATED
C_{IN}	Input Capacitance		8.0		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.7	2.9	4.5	1.7	4.5	ns
t_{PHL}	D_n to O_n	1.7	2.6	4.5	1.7	4.5	
t_{PLH}	Propagation Delay	2.6	6.0	8.5	2.6	8.5	ns
t_{PHL}	LE to O_n	2.6	4.3	8.5	2.6	8.5	
t_{PZH}	Output Enable Time	2.8	4.0	7.4	2.8	7.4	ns
t_{PZL}		2.8	5.0	7.4	2.8	7.4	
t_{PHZ}	Output Disable Time	2.2	4.0	6.3	2.2	6.3	ns
t_{PLZ}		2.2	3.5	6.3	2.2	6.3	

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	1.0	–0.4		1.0		ns
$t_S(L)$	D_n to LE	1.0	–0.7		1.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.5	0.9		2.5		ns
$t_H(L)$	D_n to LE	2.5	0.6		2.5		
$t_W(H)$	LE Pulse Width HIGH	5.0	2.7		5.0		ns

Extended AC Electrical Characteristics

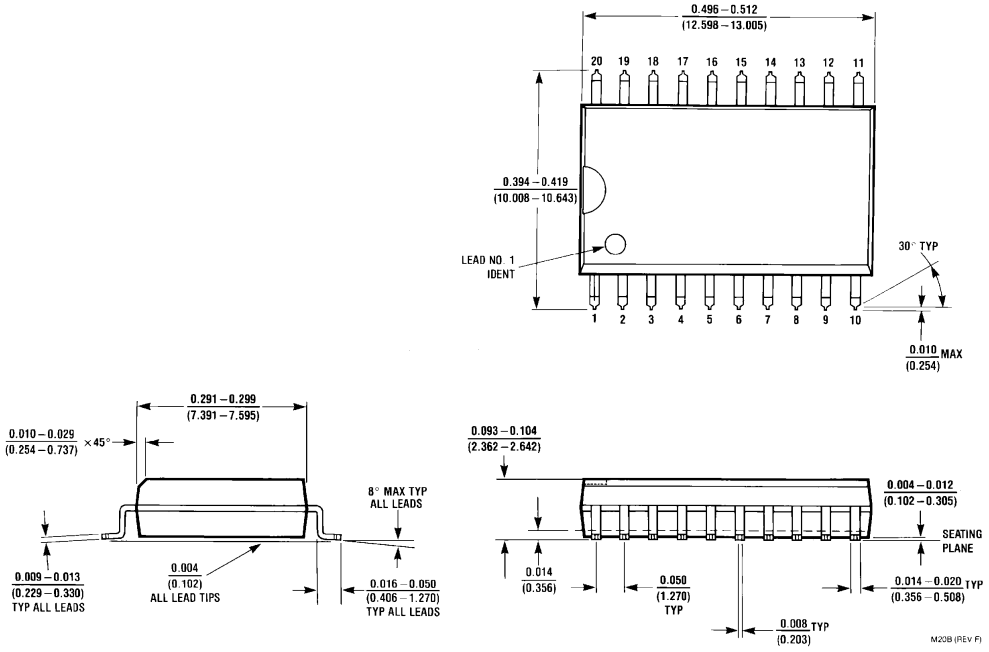
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.7	5.7	3.4	8.1	ns
t_{PHL}	D_n to O_n	1.7	5.7	3.4	8.1	
t_{PLH}	Propagation Delay	2.6	9.8	4.5	12.3	ns
t_{PHL}	LE to O_n	2.6	9.8	4.5	12.3	
t_{PZH}	Output Enable Time	2.8	9.6			ns
t_{PZL}		2.8	9.6			
t_{PHZ}	Output Disable Time	2.2	7.3			ns
t_{PLZ}		2.2	7.3			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		1.3			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.3			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.0			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e. all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

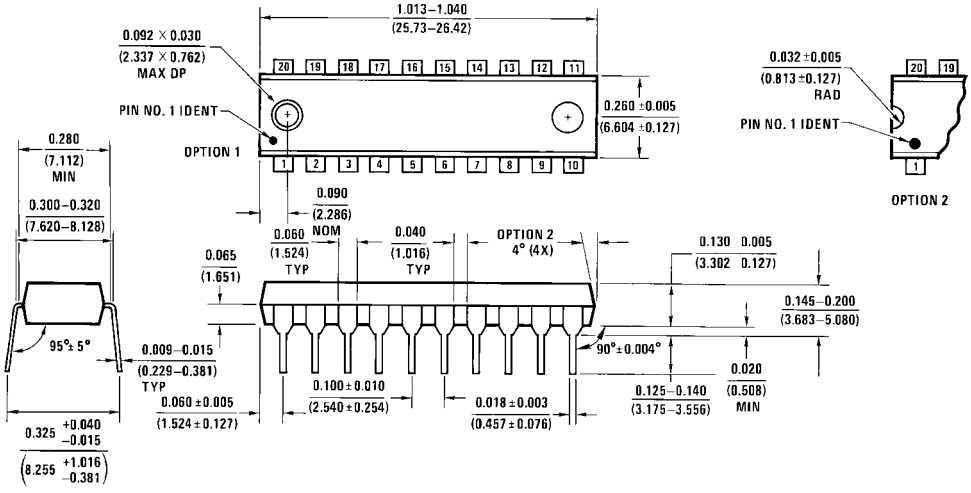
Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}) or any combination of HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

May 1992
Revised August 1999

74FR900
9-Bit, 3-Port Latchable Datapath Multiplexer

General Description

The 74FR900 is a data bus multiplexer routing any of three 9-bit ports to any other one of the three ports. Readback of data latched from any port onto itself is also possible. The 74FR900 maintains separate control of all latch-enable, output enable and select inputs for maximum flexibility. PINV allows inversion of the data from the C_8 to A_8 or B_8 path. This is useful for control of the parity bit in systems diagnostics.

Fairchild's 74FR25900 includes 25Ω resistors in series with port A and B outputs. Resistors minimize undershoot and ringing which may damage or corrupt sensitive device inputs driven by these ports.

Features

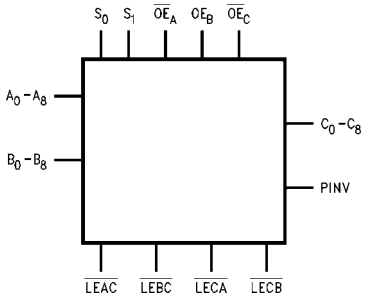
- 9-bit data ports for systems carrying parity bits
- Readback capability for system self checks.
- Independent control lines for maximum flexibility
- Guaranteed multiple output switching and 250 pF load delays
- Outputs optimized for dynamic bus drive capability
- PINV parity control facilitates system diagnostics
- FR25900 resistor option for driving MOS inputs such as DRAM arrays

Ordering Code:

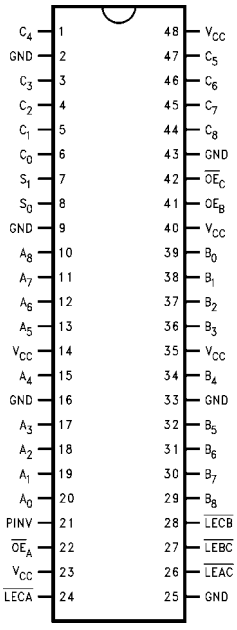
Order Number	Package Number	Package Description
74FR900SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
$\overline{LExx}$	Latch Enable Inputs
OE_x	Output Enable Inputs
PINV	Parity Invert Input
S_0, S_1	Select Inputs
A_0–A_8	Port A Inputs or 3-STATE Outputs
B_0–B_8	Port B Inputs or 3-STATE Outputs
C_0–C_8	Port C Inputs or 3-STATE Outputs

Functional Description

The 74FR900 allows 9-bit data to be transferred from any of three 9-bit I/O ports to either of the two remaining I/O ports. The device employs latches in all paths for either transparent or synchronous operation. Readback capability from any port to itself is also possible.

Data transfer within the 74FR900 is controlled through use of the select (S_0 and S_1) and output-enable ($\overline{OE}_A$, OE_B and $\overline{OE}_C$) inputs as described in Table 1. Additional control is available by use of the latch-enable inputs ($\overline{LEAC}$, $\overline{LECA}$, $\overline{LEBC}$, $\overline{LECB}$) allowing either synchronous or transparent transfers (see Table 2). Table 1 indicates several readback conditions. By latching data on a given port and initiating the readback control configuration, previous data may be read for system verification or diagnostics. This mode may be useful in implementing system diagnostics.

Data at the port to be readback must be latched prior to enabling the outputs on that port. If this is not done, a closed data loop will result causing possible data integrity problems. Note that the A and B ports allow readback without affecting any other port. Port C, however, requires interruption of either port A or B to complete its readback path.

PINV controls inversion of the C_8 bit. A low on PINV allows C_8 data to pass unaltered. A high causes inversion of the data. See Table 3. This feature allows forcing of parity errors for use in system diagnostics. This is particularly helpful in 486 processor designs as the 486 does not provide odd/even parity selection internally.

TABLE 1. Datapath Control

Inputs					Function
S_0	S_1	$\overline{OE}_A$	OE_B	$\overline{OE}_C$	
L	X	H	L	L	Port A to Port C
L	L	H	H	H	Port A to Port B
L	O	H	H	L	Port A to B+C
H	L	L	L	H	Port B to Port A
H	X	H	L	L	Port B to Port C
H	O	L	L	L	Port B to A+C
X	H	L	L	H	Port C to Port A
X	H	H	H	H	Port C to Port B
X	H	L	H	H	Port C to A+B
X	X	H	L	H	Outputs Disabled
L	L	L	X	X	(Readback to A) (Note 1)
L	H	L	X	L	(Readback to A or C) (Note 1)
H	L	X	H	X	(Readback to B) (Note 1)
H	H	X	H	L	(Readback to B or C) (Note 1)

Note 1: Readback operation in latched mode only. Transparent operation could result in unpredictable results.

TABLE 2. Latch-Enable Control

$\overline{LExx}$	Input	Output
L	L	L
L	H	H
H	X	Q_0

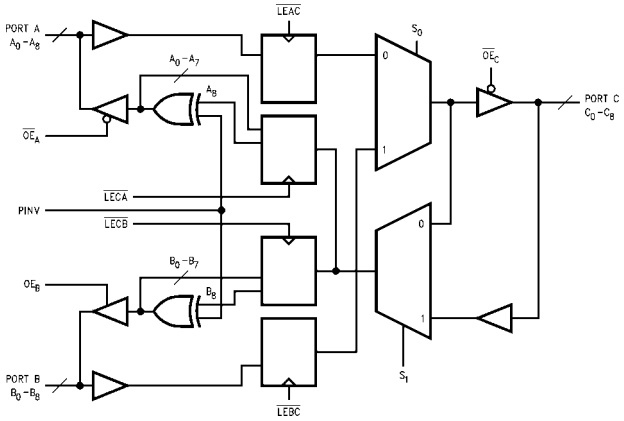
L = LOW Voltage H = HIGH Voltage Level

TABLE 3. PINV Control

PINV	C_8	A_8 or B_8
L	L	L
L	H	H
H	L	H
H	H	L

Q_0 = Output state prior to $\overline{LExx}$ LOW-to-HIGH transition

Logic Diagram



Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n, C_n)
		2.0			V	Min	I_{OH} = −15 mA (A_n, B_n, C_n)
V_{OL}	Output LOW Voltage			0.50	V	Min	I_{OL} = 24 mA (A_n, B_n, C_n)
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V (Control Inputs)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V (Control Inputs)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n, C_n)
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5V (Control Inputs)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Test			3.75	V	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
$I_{IH} + I_{OZH}$	Output Leakage Current			25	µA	Max	V_{OUT} =2.7V (A_n, B_n, C_n)
$I_{IIL} + I_{OZL}$	Output Leakage Current			−150	µA	Max	V_{OUT} = 0.5V (A_n, B_n, C_n)
I_{OS}	Output Short Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V (A_n, B_n, C_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n, C_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n, C_n)
I_{CCH}	Power Supply Current		115	150	mA	Max	All Outputs HIGH (Note 4)
I_{CCL}	Power Supply Current		170	200	mA	Max	All Outputs LOW (Note 4)
I_{CCZ}	Power Supply Current		147	175	mA	Max	Outputs in 3-STATE

Note 4: 2 ports active only

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay A_n or B_n to C_n C_n to A_n or B_n	2.0	4.2	7.0	2.0	7.0	ns
t_{PLH} t_{PHL}	Propagation Delay C_8 to A_8 or B_8 (PINV HIGH)	2.5	4.8	7.5	2.5	7.5	ns
t_{PLH} t_{PHL}	Propagation Delay A_n to B_n, B_n to A_n	4.5	6.4	10.0	4.5	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEAC}$ to C_n, $\overline{LEBC}$ to C_n	4.5	6.8	10.0	4.5	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LECA}$ to A_n, $\overline{LECB}$ to B_n	3.0	6.0	9.5	3.0	9.5	ns
t_{PLH} t_{PHL}	Propagation Delay S_0 to C_n	3.0	6.0	10.0	3.0	10.0	ns
t_{PLH} t_{PHL}	Propagation Delay S_1 to A_n or B_n	3.5	6.5	11.0	3.5	11.0	ns
t_{PLH} t_{PHL}	Propagation Delay PINV to A_8 or B_8	2.0	5.0	9.0	2.0	9.0	ns
t_{PZH} t_{PZL}	Output Enable Time A_n, C_n	2.0	4.0	6.5	2.0	6.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time A_n, C_n	1.5	4.0	6.0	1.5	6.0	ns
t_{PZH} t_{PZL}	Output Enable Time B_n	2.0	5.0	7.0	2.0	7.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time B_n	2.0	5.0	7.0	2.0	7.0	ns

AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW A_n to $\overline{LEAC}$, B_n to $\overline{LEBC}$	4.0	2.0		4.0		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW A_n to $\overline{LEAC}$, B_n to $\overline{LEBC}$	1.0	–2.0		1.0		ns
$t_S(H)$ $t_S(L)$	Setup Time, HIGH or LOW C_n to $\overline{LECA}$ or $\overline{LECB}$	3.0	1.0		3.0		ns
$t_H(H)$ $t_H(L)$	Hold Time, HIGH or LOW C_n to $\overline{LECA}$ or $\overline{LECB}$	1.0	–1.0		1.0		ns
$t_W(H)$	$\overline{LE}$ Pulse Width LOW	8.0	4.0		8.0		ns

Extended AC Electrical Characteristics

Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Nine Outputs Switching (Note 5)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 6)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay					

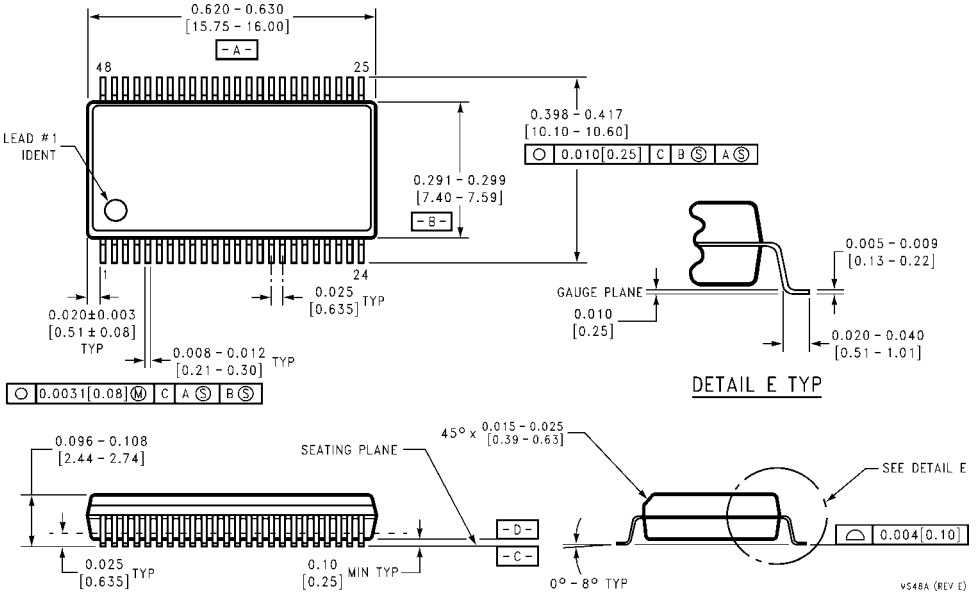
Extended AC Electrical Characteristics (Continued)

Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Nine Outputs Switching (Note 5)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 6)		Units
		Min	Max	Min	Max	
t_{PHL}	A_n or B_n to C_n C_n to A_n or B_n	2.0	9.0	2.5	10.5	ns
t_{PLH} t_{PHL}	Propagation Delay C_8 to A_8 or B_8 (PINV HIGH)			3.5	11.0	ns
t_{PLH} t_{PHL}	Propagation Delay A_n to B_n, B_n to A_n	4.5	12.0	5.5	13.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LEAC}$ to C_n, $\overline{LEBC}$ to C_n	4.5	12.0	5.5	13.5	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{LECA}$ to A_n, $\overline{LECB}$ to B_n	3.0	11.5	4.0	13.5	ns
t_{PLH} t_{PHL}	Propagation Delay S_0 to C_n	3.0	11.0	3.0	14.0	ns
t_{PLH} t_{PHL}	Propagation Delay S_1 to A_n or B_n	3.5	12.0	4.5	15.0	ns
t_{PLH} t_{PHL}	Propagation Delay PINV to A_8 or B_8			2.5	12.0	ns
t_{PZH} t_{PZL}	Output Enable Time A_n, C_n	2.0	8.0			ns
t_{PHZ} t_{PLZ}	Output Disable Time A_n, C_n	1.5	6.0			ns
t_{PZH} t_{PZL}	Output Enable Time B_n	2.0	8.0			ns
t_{PHZ} t_{PLZ}	Output Disable Time B_n	2.0	7.0			ns

Note 5: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 6: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors standard AC load. This specification pertains to single output switching only.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS48A

FAIRCHILD SEMICONDUCTOR™

April 1991
Revised August 1999

74FR9240
9-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The 74FR9240 is an inverting 9-bit buffer and line driver designed to be employed as memory and address driver, clock driver and bus oriented transmitter or receiver.

Features

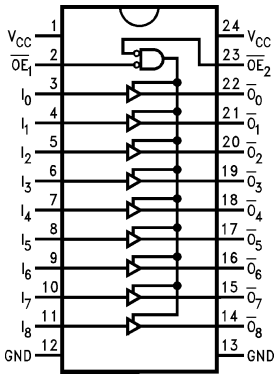
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 64 mA and source 15 mA
- Guaranteed multiple output switching, 250 pF delay and pin-to-pin skew
- Guaranteed 4000V minimum ESD protection
- 9-bit architecture for systems carrying parity

Ordering Code:

Order Number	Package Number	Package Description
74FR9240SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR9240SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Description

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active-LOW)
I_0–I_8	Inputs
$\overline{O}_0$–$\overline{O}_8$	Outputs

Truth Table

$\overline{OE}_1$	$\overline{OE}_2$	I_n	$\overline{O}_n$
H	X	X	Z
X	H	X	Z
L	L	H	L
L	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice the Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA
		2.0			V	Min	I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			−150	µA	Max	V_{IN} = 0.5V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			−20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		9	13	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		37	45	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		31	38	mA	Max	Outputs 3-STATE
C_{IN}	Input Capacitance		8.0		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	3.3	4.5	1.0	4.5	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	2.9	4.5	1.0	4.5	
t_{PZH}	Output Enable Time	2.6	4.0	6.6	2.6	6.6	ns
t_{PZL}		2.6	6.3	6.6	2.6	6.6	
t_{PHZ}	Output Disable Time	1.7	3.3	6.2	1.7	6.2	ns
t_{PLZ}		1.7	2.9	6.2	1.7	6.2	

Extended AC Electrical Characteristics

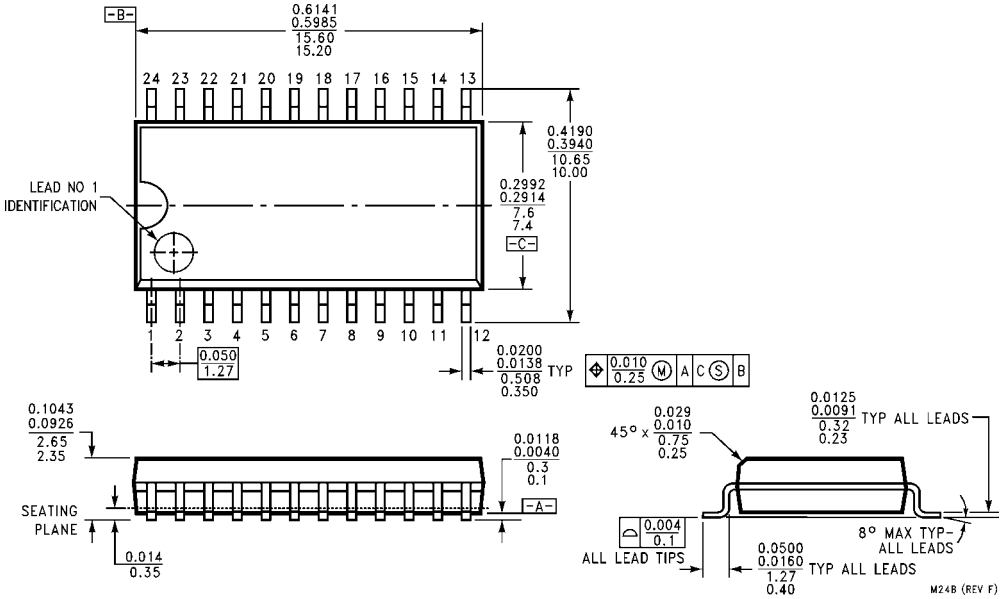
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	6.0	2.3	8.3	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	6.0	2.3	8.3	
t_{PZH}	Output Enable Time	2.6	7.2			ns
t_{PZL}		2.6	7.2			
t_{PHZ}	Output Disable Time	1.7	6.6			ns
t_{PLZ}		1.7	6.6			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		2.0			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.1			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.0			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

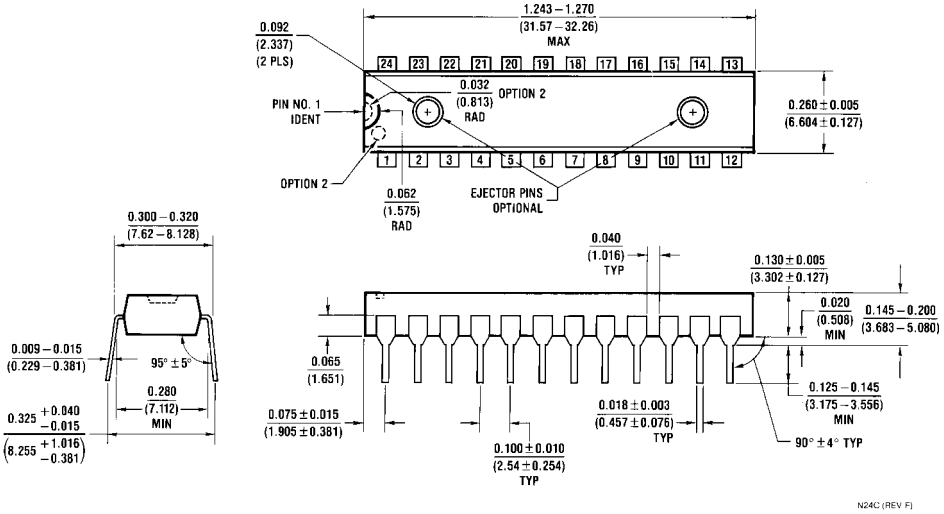
Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

April 1991
Revised August 1999

74FR9244
9-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The 74FR9244 is a non-inverting 9-bit buffer and line driver designed to be employed as memory and address driver, clock driver and bus-oriented transmitter/receiver.

Features

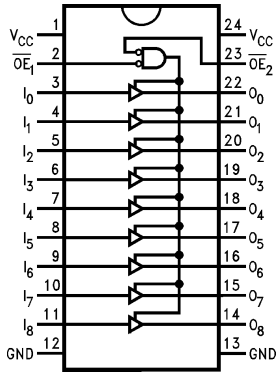
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs sink 64 mA and source 15 mA
- Guaranteed multiple output switching, 250 pf delays and pin-to-pin skew
- Guaranteed 4000V minimum ESD protection
- 9-Bit architecture for systems carrying parity

Ordering Code:

Order Number	Package Number	Package Description
74FR9244SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR9244SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$,–$\overline{OE}_2$	Output Enable Input (Active-LOW)
I_0–I_8	Inputs
O_0–O_8	Outputs

Truth Table

$\overline{OE}_1$	$\overline{OE}_2$	I_n	O_n
H	X	X	Z
X	H	X	Z
L	L	H	H
L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Storage Temperature	–65°C to +150°C
Ambient Temperature Under Bias	–55°C to +125°C
Junction Temperature Under Bias	–55°C to +150°C
V_{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
Input Voltage (Note 2)	–0.5V to +7.0V
Input Current (Note 2)	–30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	–0.5V to V_{CC}
3-STATE Output	–0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	Twice The Rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			–1.2	V	Min	I_{IN} = –18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = –3 mA
		2.0			V	Min	I_{OH} = –15 mA
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current			–150	µA	Max	V_{IN} = 0.5V
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA, All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV, All Other Pins Grounded
I_{OZH}	Output Leakage Current			20	µA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current			–20	µA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current	–100		–225	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current		30	40	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		60	75	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		35	45	mA	Max	Outputs 3-STATED
C_{IN}	Input Capacitance		8.0		pF	5.0	

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.6	4.1	1.0	4.1	ns
t_{PHL}		1.0	1.8	4.1	1.0	4.1	
t_{PZH}	Output Enable Time	2.6	4.8	7.0	2.6	7.0	ns
t_{PZL}		2.6	3.9	7.0	2.6	7.0	
t_{PHZ}	Output Disable Time	1.6	3.7	6.1	1.6	6.1	ns
t_{PLZ}		1.6	3.6	6.1	1.6	6.1	

Extended AC Characteristics

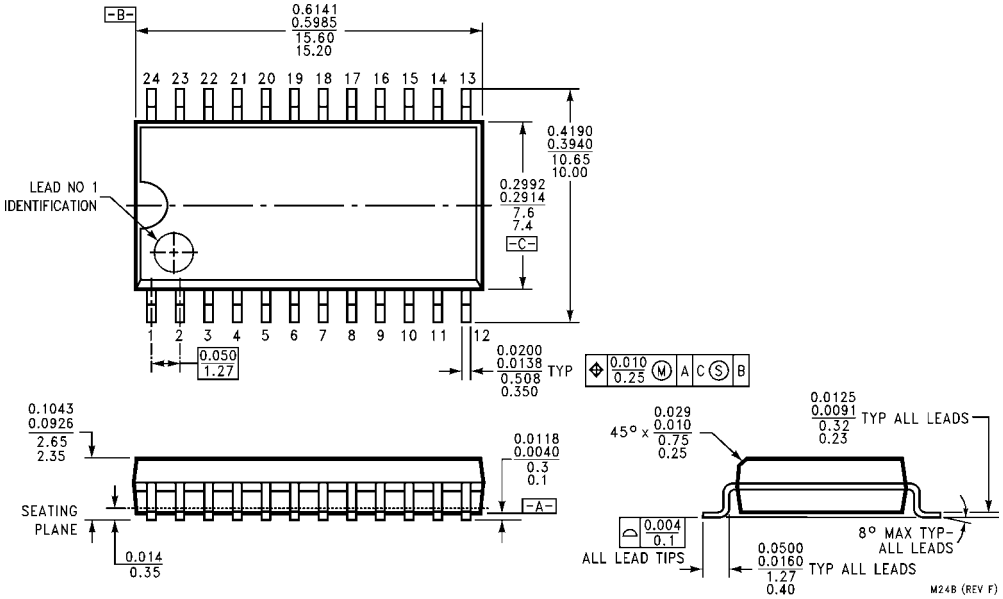
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	6.0	2.3	8.0	ns
t_{PHL}		1.0	6.0	2.3	8.0	
t_{PZH}	Output Enable Time	2.6	8.5			ns
t_{PZL}		2.6	8.5			
t_{PHZ}	Output Disable Time	1.6	6.5			ns
t_{PLZ}		1.6	6.5			
t_{OSHL}	Pin-to-Pin Skew for HL Transitions (Note 5)		1.3			ns
t_{OSLH}	Pin-to-Pin Skew for LH Transitions (Note 5)		1.7			ns
t_{OST}	Pin-to-Pin Skew for HL/LH Transitions (Note 5)		3.0			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

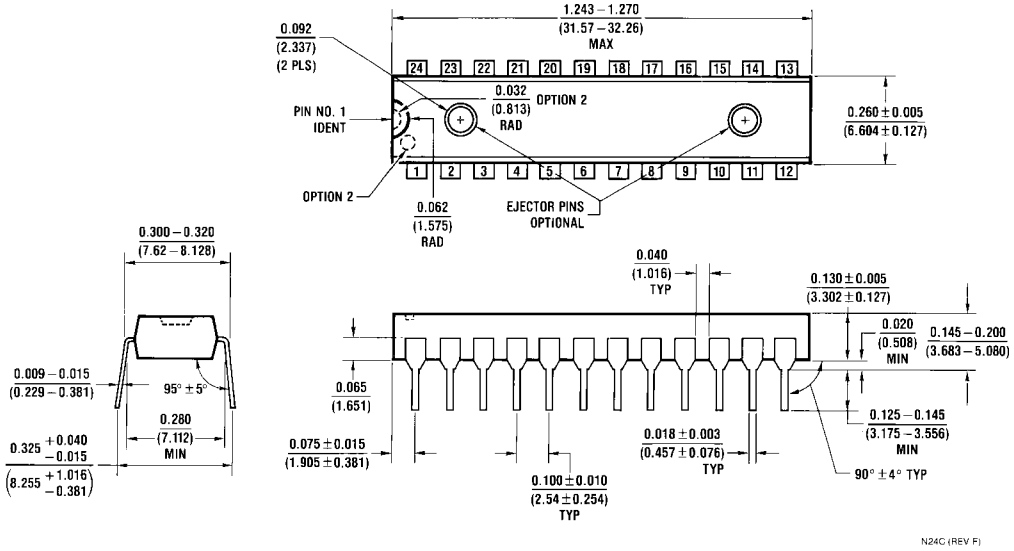
Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW, (t_{OSHL}), LOW-to-HIGH, (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH, (t_{OST}). Specification guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

FAIRCHILD SEMICONDUCTOR™

April 1991
Revised August 1999

74FR9245
9-Bit Bidirectional Transceiver with 3-STATE Outputs

General Description

The 74FR9245 contains nine non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 64 mA on both the A and B Ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a High Z condition.

Features

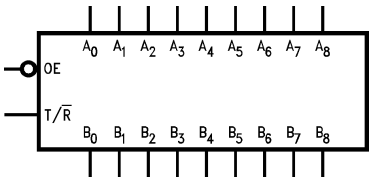
- Non-inverting buffers
- Bidirectional data path
- A and B output sink capability of 64 mA, source capability of 15 mA
- Guaranteed pin-to-pin skew, multiple output switching and 250 pf delay

Ordering Code:

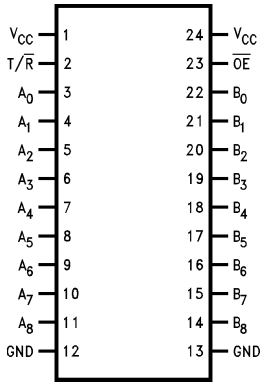
Order Number	Package Number	Package Description
74FR9245SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74FR9245MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74FR9245SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

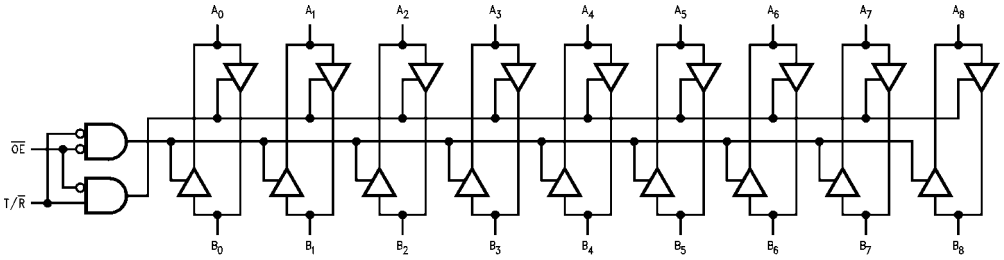
Pin Names	Description
$\overline{OE}$	Output Enable Input (Active-LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_8	Side A Inputs or 3-STATE Outputs
B_0–B_8	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Output
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 1: Absolute maximum ratings are value beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW Voltage			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5	µA	Max	V_{IN} = 2.7V ($\overline{OE}$, T/$\overline{R}$)
I_{BVI}	Input HIGH Current Breakdown Test			7	µA	Max	V_{IN} = 7.0V ($\overline{OE}$, T/$\overline{R}$)
I_{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	µA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{IL}	Input LOW Current			−250	µA	Max	V_{IN} = 0.5V ($\overline{OE}$, T/$\overline{R}$)
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Circuit Leakage Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
$I_{IH} + I_{OZH}$	Output Leakage Current			25	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
$I_{IL} + I_{OZL}$	Output Leakage Current			−150	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0.0V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC} (A_n, B_n)
I_{ZZ}	Bus Drainage Test			100	µA	0.0	V_{OUT} = 5.25V (A_n, B_n)
I_{CCH}	Power Supply Current		55	80	mA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current		75	115	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current		65	85	mA	Max	Outputs 3-STATE
C_{IN}	Input Capacitance		8.0		pF	5.0	$\overline{OE}$, T/$\overline{R}$
			17.0		pF	5.0	A_n, B_n

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			$T_A = 0°C$ to $+70°C$, $V_{CC} = +50V$, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	2.6	3.9	1.0	3.9	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	1.7	3.9	1.0	3.9	
t_{PZH}	Output Enable Time	2.7	5.0	6.5	2.7	6.5	ns
t_{PZL}		2.7	4.3	6.5	2.7	6.5	
t_{PHZ}	Output Disable Time	1.7	3.7	6.0	1.7	6.0	ns
t_{PLZ}		1.7	3.6	6.0	1.7	6.0	

Extended AC Electrical Characteristics

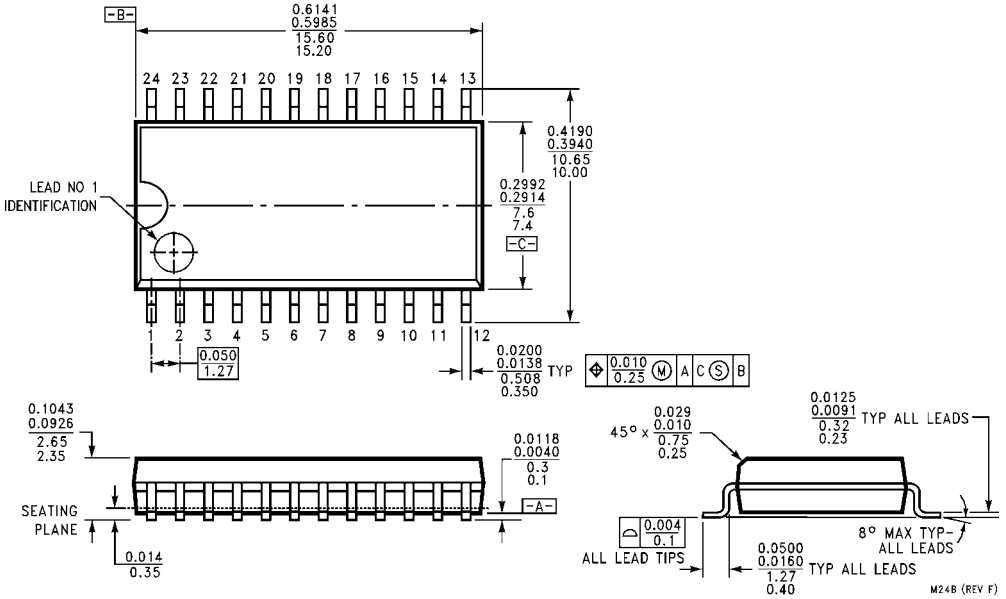
Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = +50V$, $C_L = 50$ pF, Eight Outputs Switching (Note 3)		$T_A = 0°C$ to $+70°C$, $V_{CC} = +50V$, $C_L = 250$ pF (Note 4)		Units
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.0	5.8	2.2	8.1	ns
t_{PHL}	A_n to B_n or B_n to A_n	1.0	5.8	2.2	8.1	
t_{PZH}	Output Enable Time	2.7	8.8			ns
t_{PZL}		2.7	8.8			
t_{PHZ}	Output Disable Time	1.7	7.0			ns
t_{PLZ}		1.7	7.0			
t_{OSHL} (Note 5)	Pin-to-Pin Skew for HL Transitions		2.0			ns
t_{OSLH} (Note 5)	Pin-to-Pin Skew for LH Transitions		1.0			ns
t_{OST} (Note 5)	Pin-to-Pin Skew for HL/LH Transitions		3.0			ns

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase, i.e., all LOW-to-HIGH, HIGH-to-LOW, 3-STATE-to-HIGH, etc.

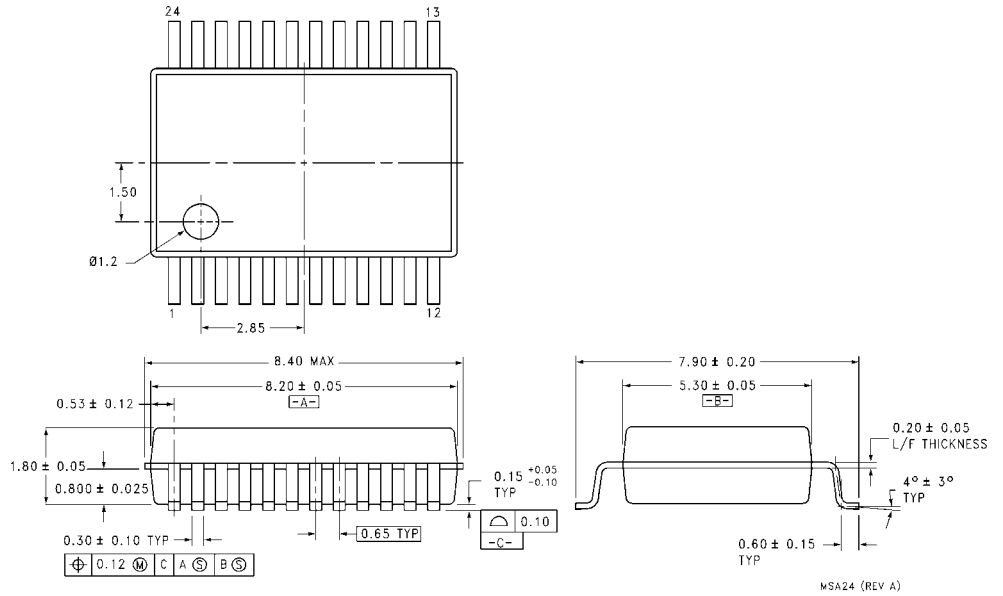
Note 4: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delays for any two outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t_{OSHL}), LOW-to-HIGH (t_{OSLH}), or HIGH-to-LOW and/or LOW-to-HIGH (t_{OST}). Specifications guaranteed with all outputs switching in phase.

Physical Dimensions inches (millimeters) unless otherwise noted

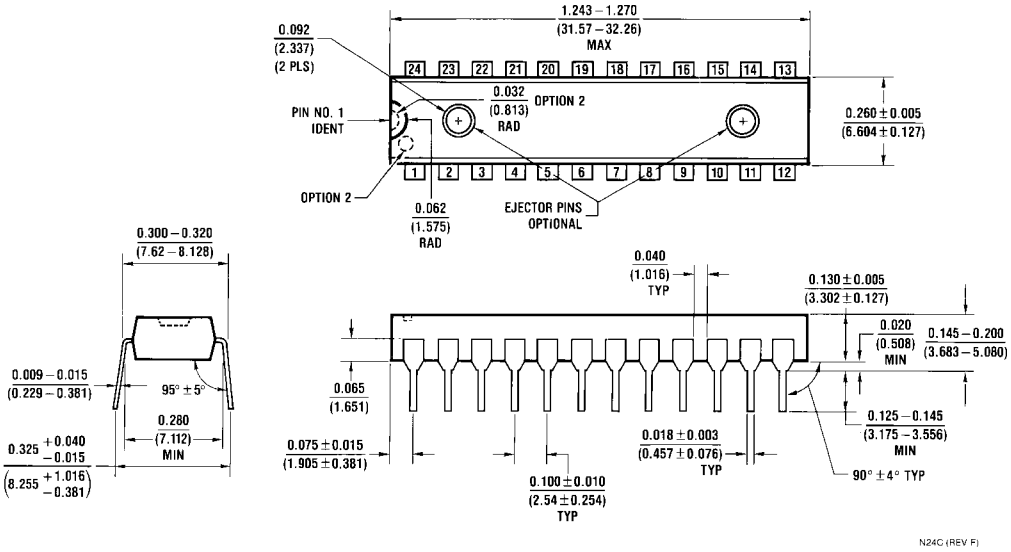


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-100, 0.300 Wide
Package Number N24C

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised March 1999

74LCX00
Low Voltage Quad 2-Input NAND Gate with 5V Tolerant Inputs

General Description

The LCX00 contains four 2-input NAND gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX00 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

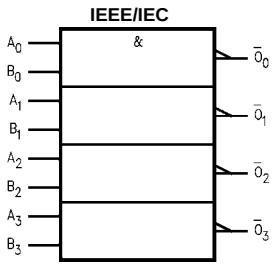
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.2 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

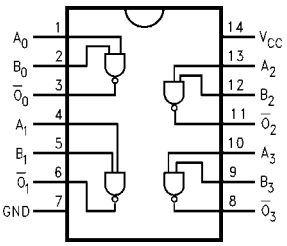
Order Number	Package Number	Package Description
74LCX00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V - 3.0V		±12	
		V_{CC} = 2.3V - 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = –40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = –8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50pF$		$C_L = 50pF$		$C_L = 30pF$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.2	1.5	6.0	1.5	6.2	ns
t_{PLH}		1.5	5.2	1.5	6.0	1.5	6.2	
t_{OSHL}	Output to Output Skew (Note 4)		1.0					ns
t_{OSLH}			1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Unit
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

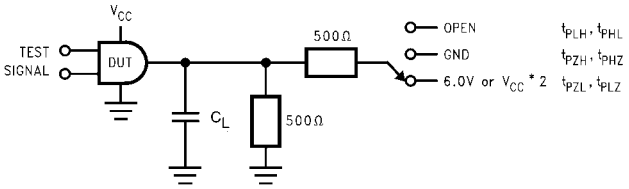
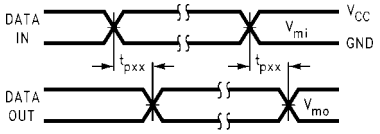
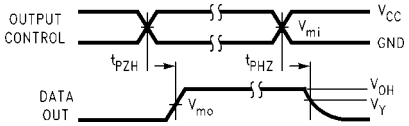


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

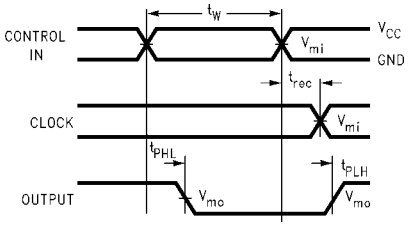
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



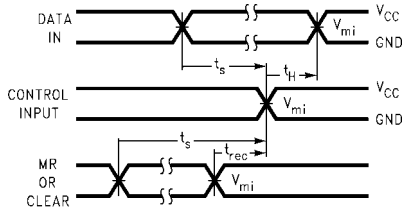
Waveform for Inverting and Non-Inverting Functions



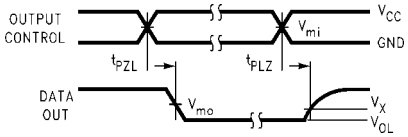
3-STATE Output High Enable and Disable Times for Logic



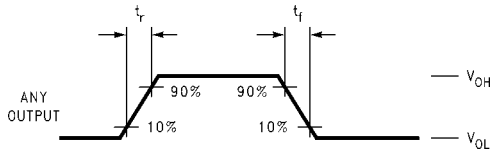
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

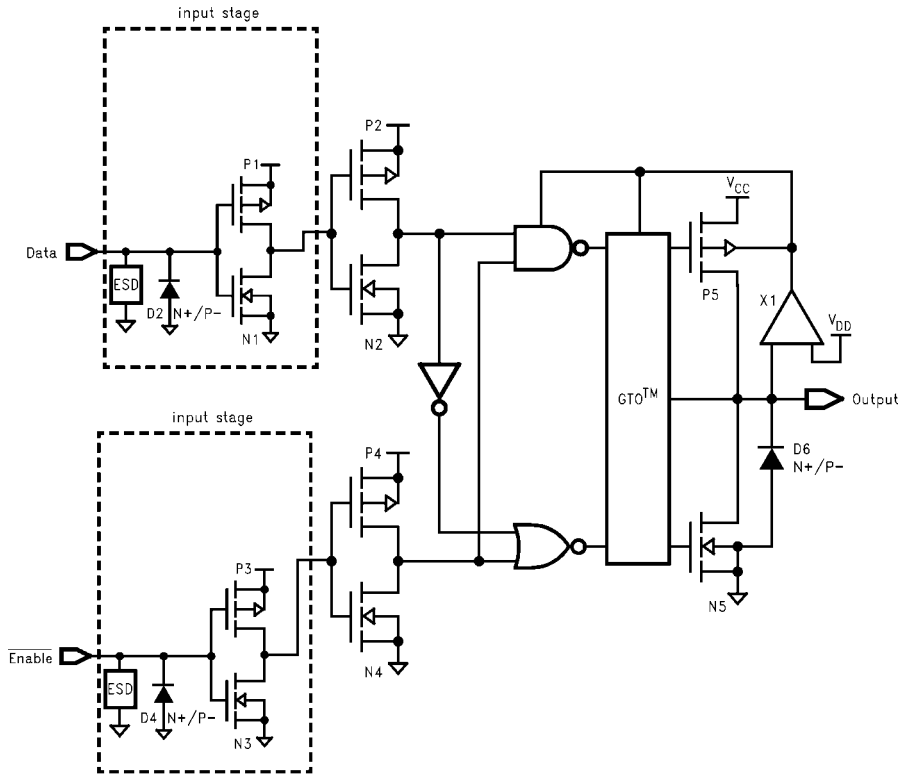


t_{rise} and t_{fall}

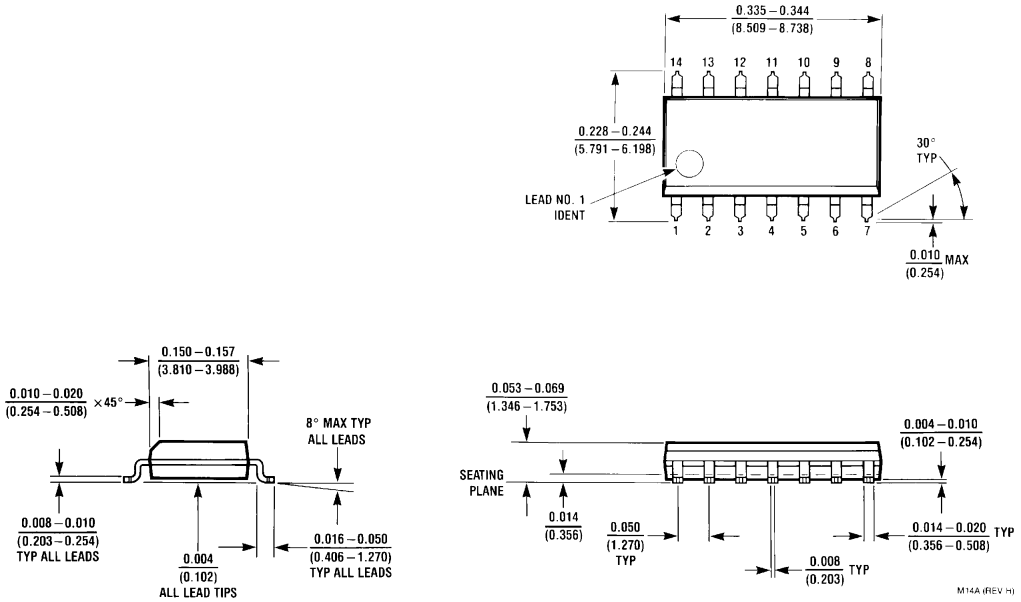
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

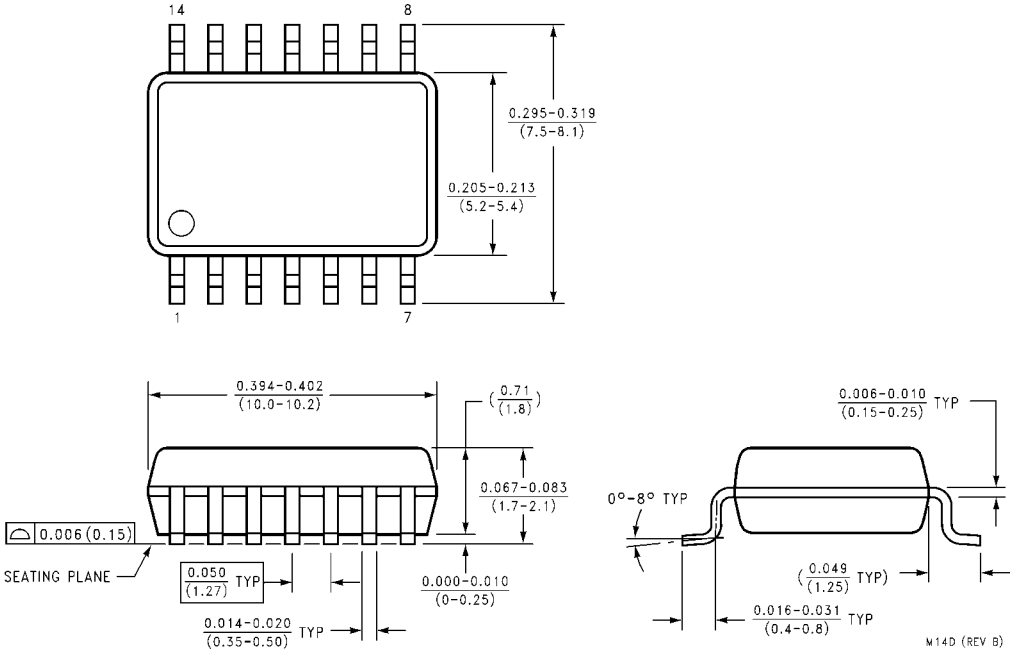
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

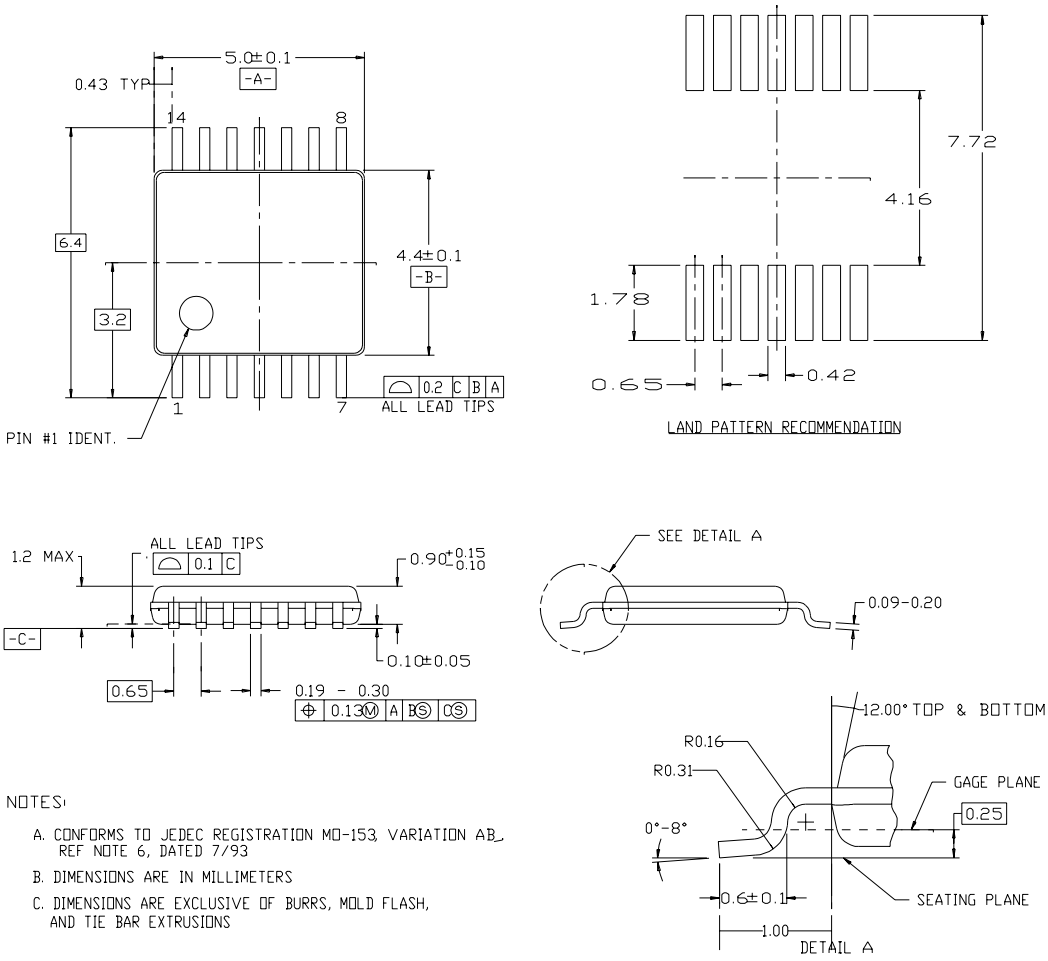


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

March 1995
Revised June 1999

74LCX02
Low Voltage Quad 2-Input NOR Gate with 5V Tolerant Inputs

General Description

The LCX02 contains four 2-input NOR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX02 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

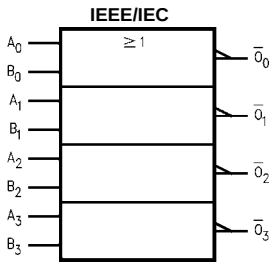
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specification provided
- 5.2 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

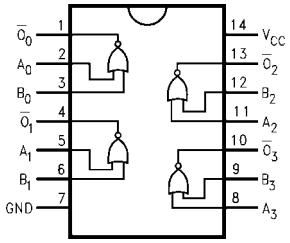
Order Number	Package Number	Package Description
74LCX02M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those beyond which the safety of the device cannot be guaranteed. The device should not be operating at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$,		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay Time	1.5	5.2	1.5	6.0	1.5	6.2	ns
t_{PLH}		1.5	5.2	1.5	6.0	1.5	6.2	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

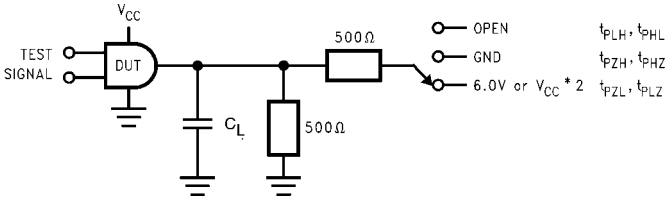
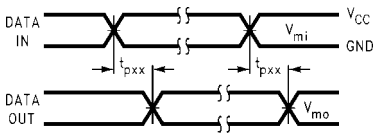
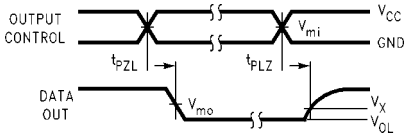


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

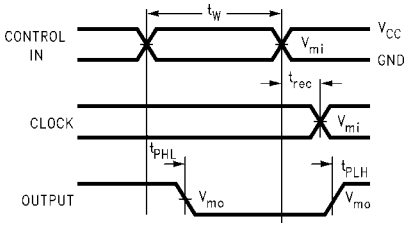
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



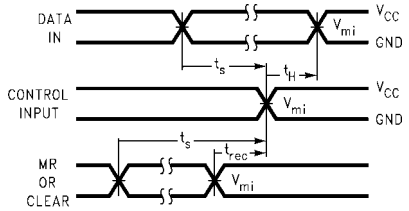
Waveform for Inverting and Non-Inverting Functions



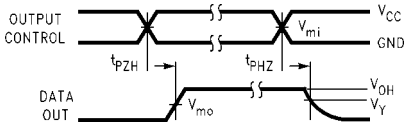
3-STATE Output Low Enable and Disable Times for Logic



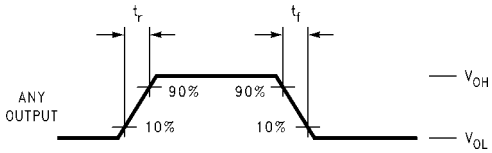
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

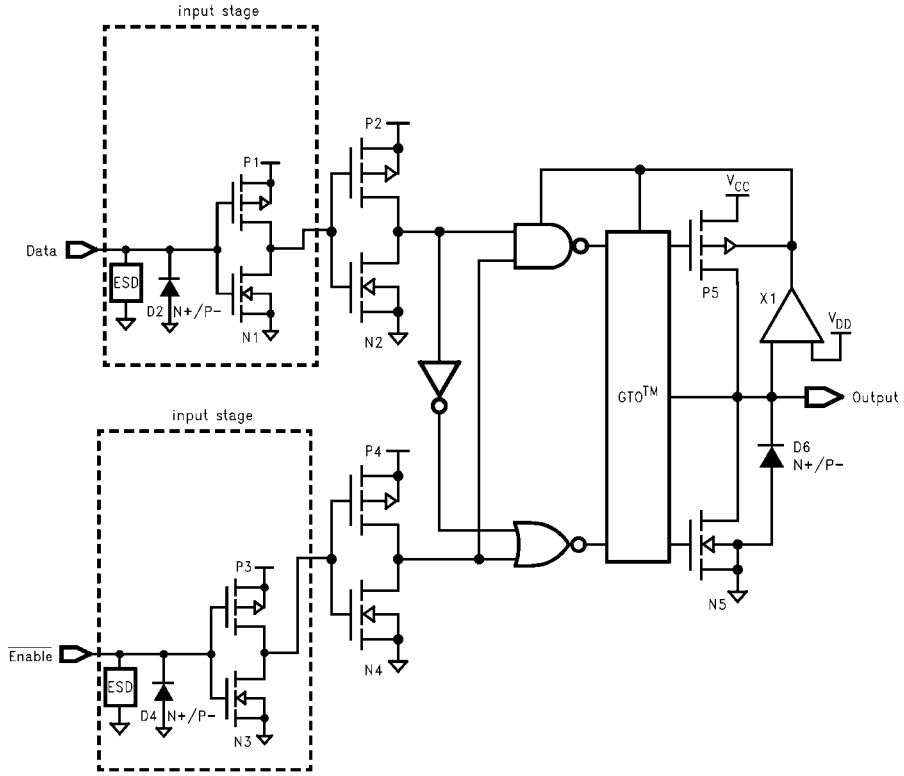


t_{rise} and t_{fall}

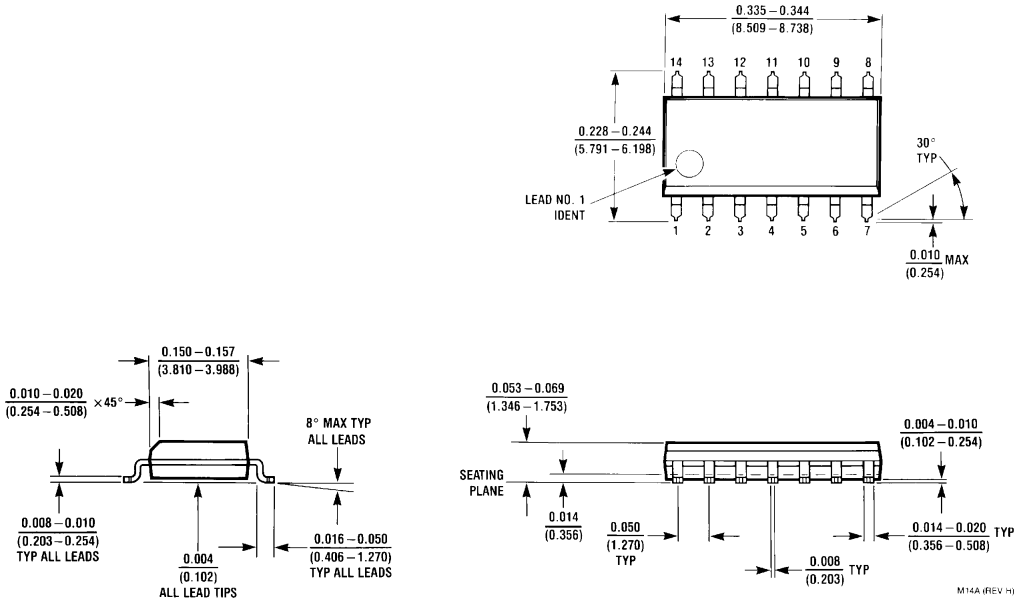
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

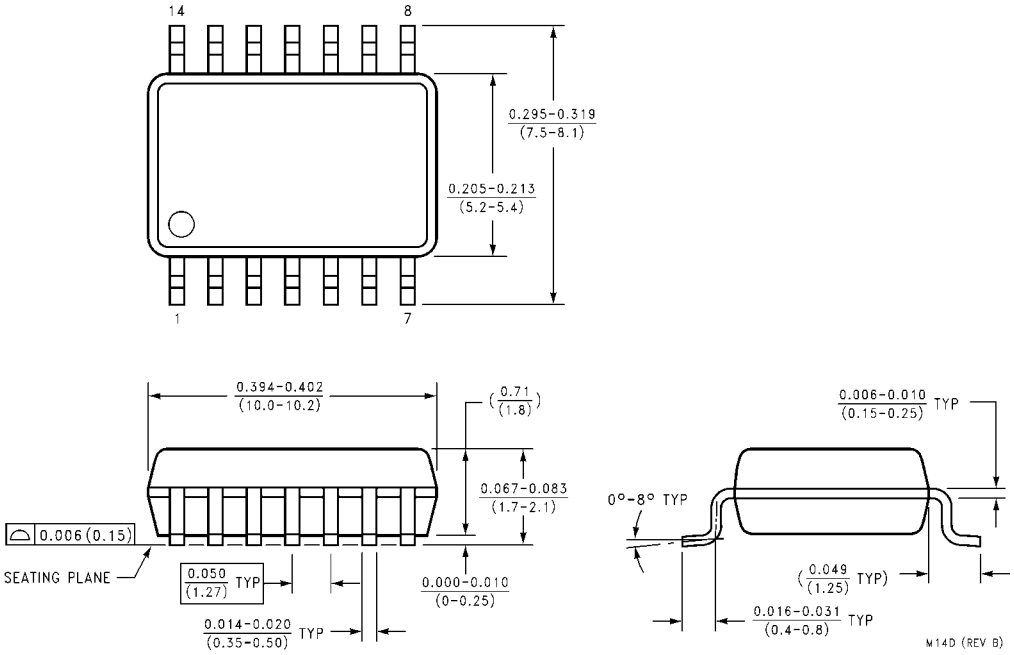
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

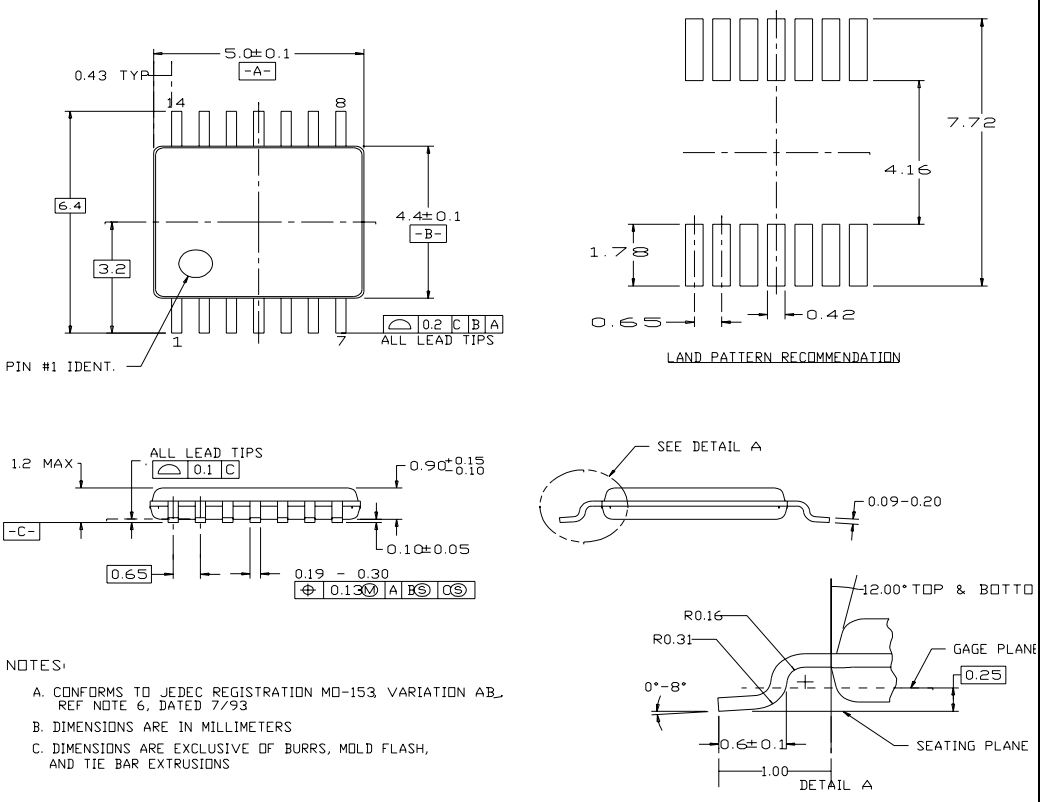


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

March 1995
Revised May 1999

74LCX04
Low Voltage Hex Inverter with 5V Tolerant Inputs

General Description

The LCX04 contains six inverters. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX04 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

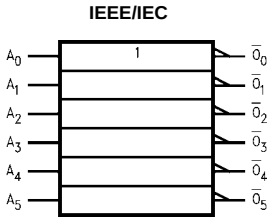
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.2 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

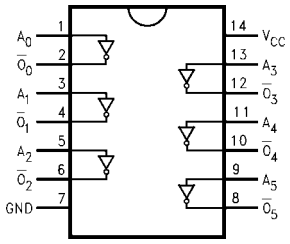
Order Number	Package Number	Package Description
74LCX04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = 24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = −100 μA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	μA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	μA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.3 – 3.6		500	μA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay Time	1.5	5.2	1.5	6.0	1.5	6.2	ns
t_{PLH}		1.5	5.2	1.5	6.0	1.5	6.2	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (T_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

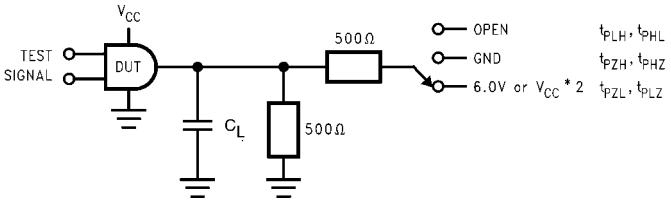
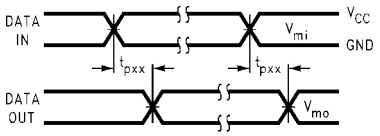
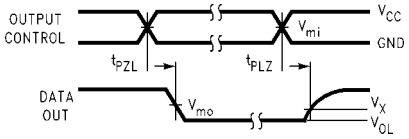


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

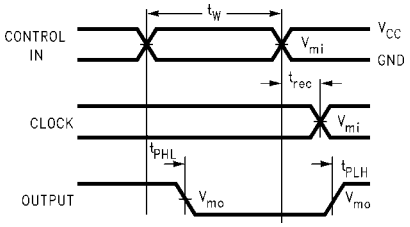
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



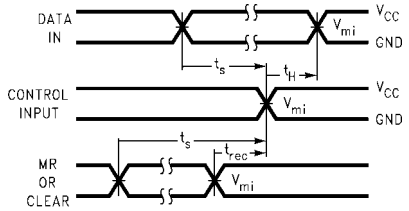
Waveform for Inverting and Non-Inverting Functions



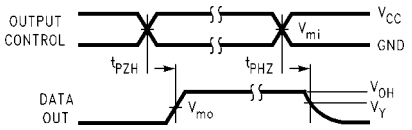
3-STATE Output Low Enable and Disable Times for Logic



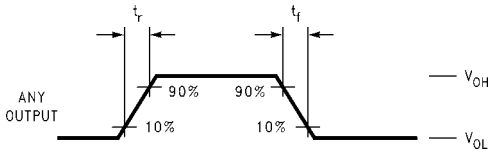
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

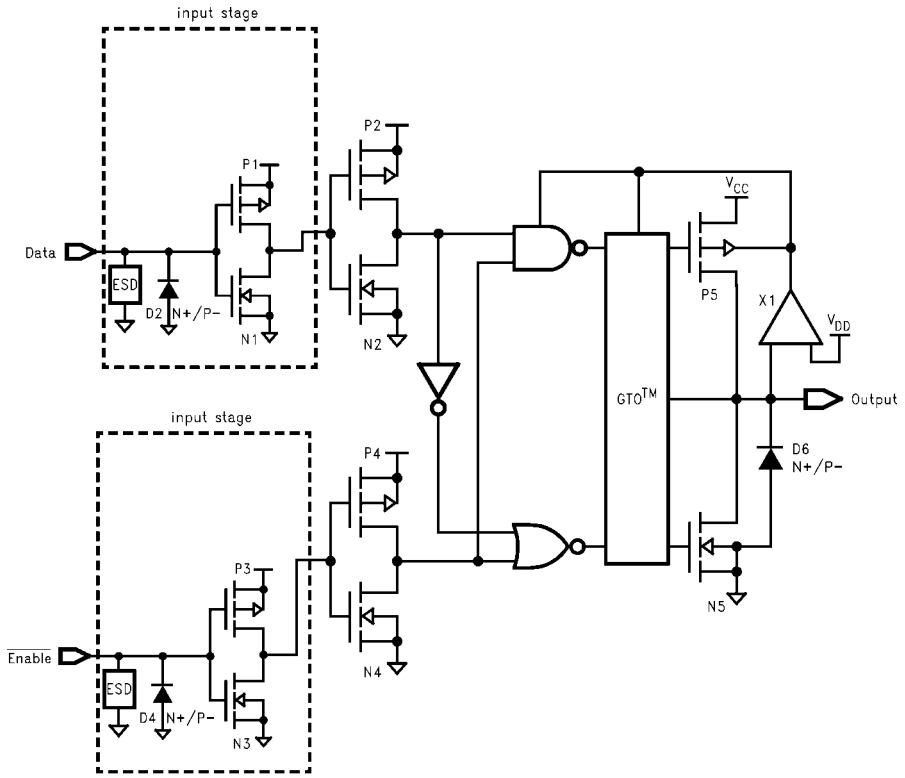


t_{rise} and t_{fall}

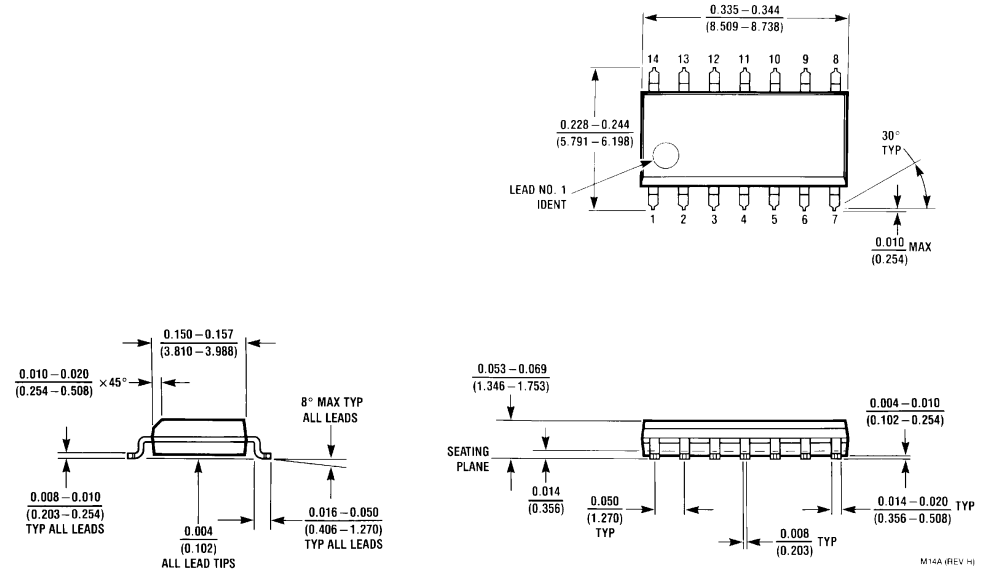
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

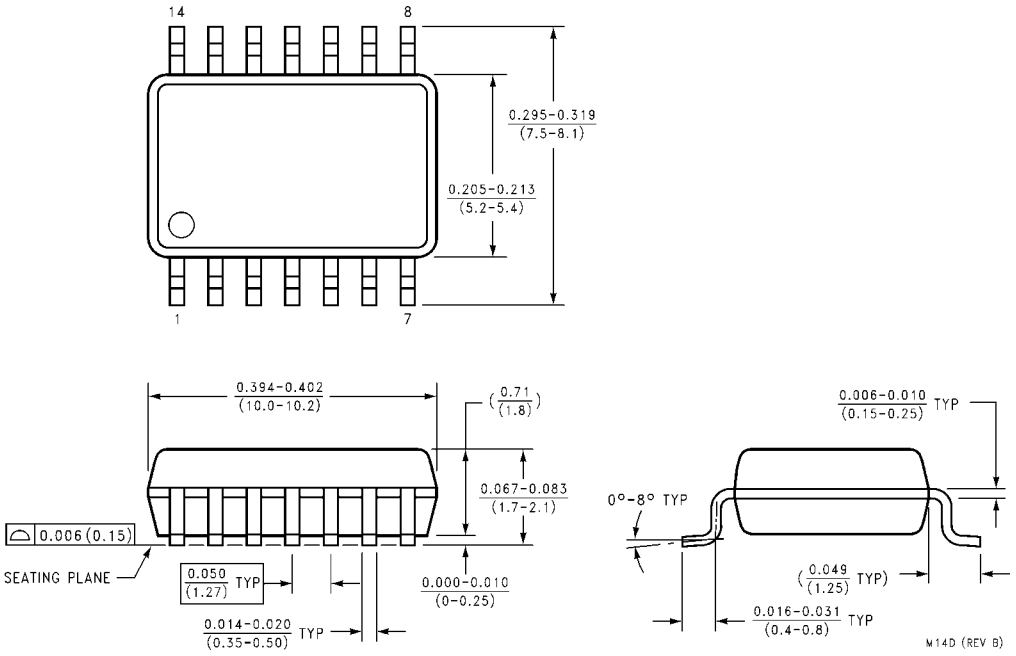
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted



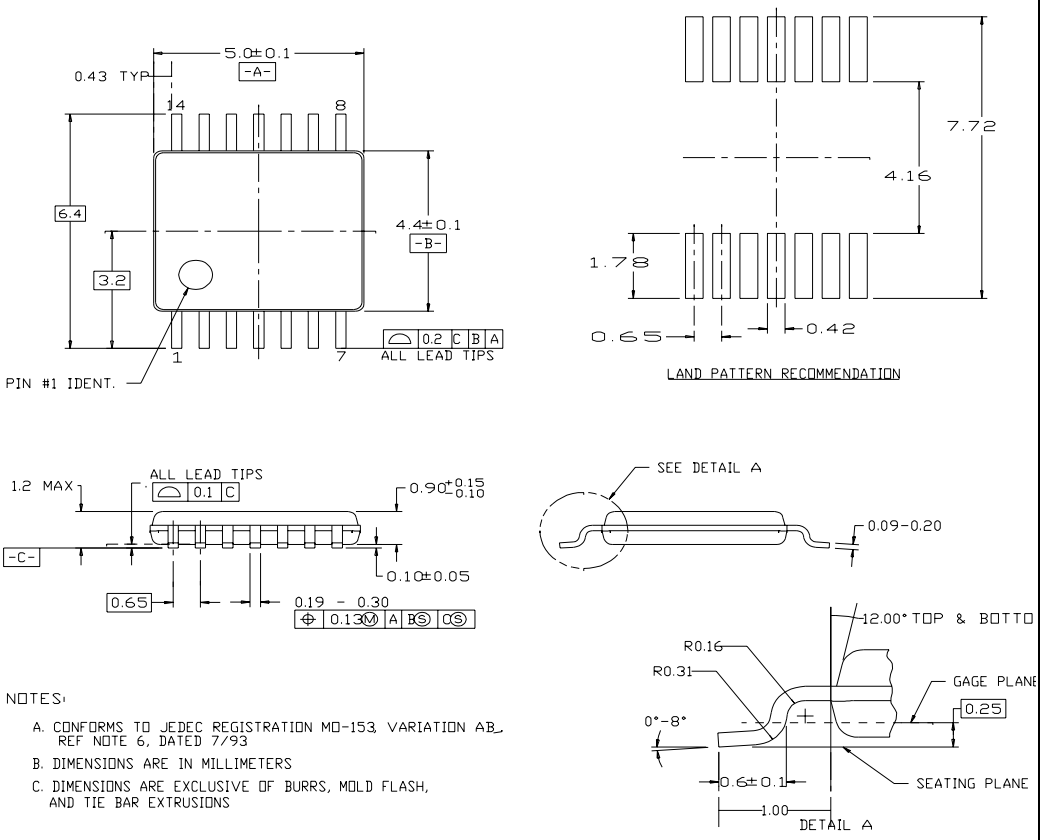
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

October 1999
Revised October 1999

74LCX06
Low Voltage Hex Inverter/Buffer with Open Drain Outputs

General Description

The LCX06 contains six inverters/buffers. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The outputs of the LCX06 are open drain and can be connected to other open drain outputs to implement active LOW wire AND or active HIGH wire OR functions.

The 74LCX06 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

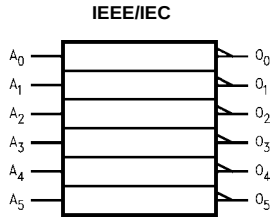
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 3.7 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- Functionally compatible with 74 series 05
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

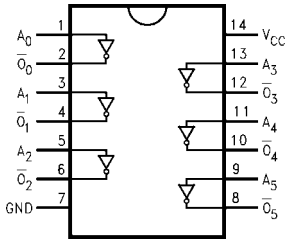
Order Number	Package Number	Package Description
74LCX06M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX06SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX06MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = –40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OL}	LOW Level Output Voltage	I_{OL} = –100 μA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	μA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	μA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	μA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PZL}	Propagation Delay Time	0.8	3.7	1.0	4.1	0.8	3.5	ns
t_{PLZ}		0.8	3.7	1.0	4.1	0.8	3.5	

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.9	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.7	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

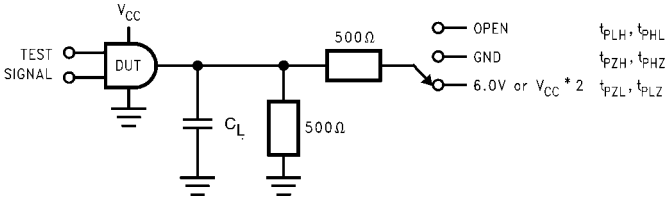
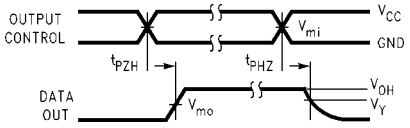
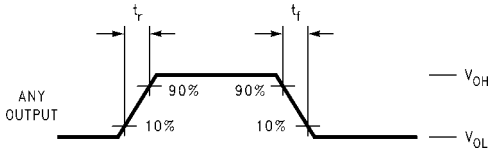


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

Test	Switch
t_{PLH}, t_{PHL}	OPEN
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



3-STATE Output High Enable and Disable TImes for Logic

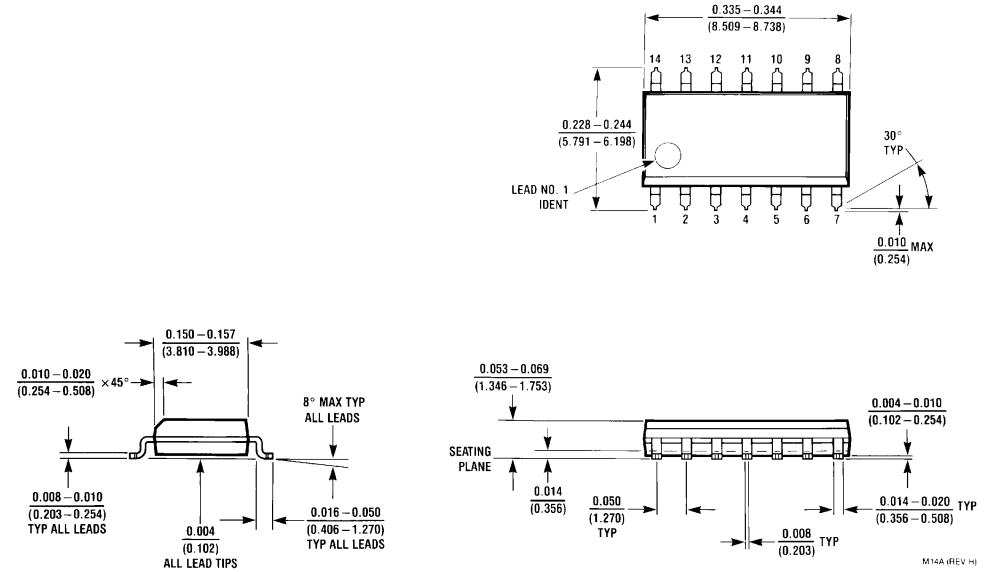


t_{rise} and t_{fall}

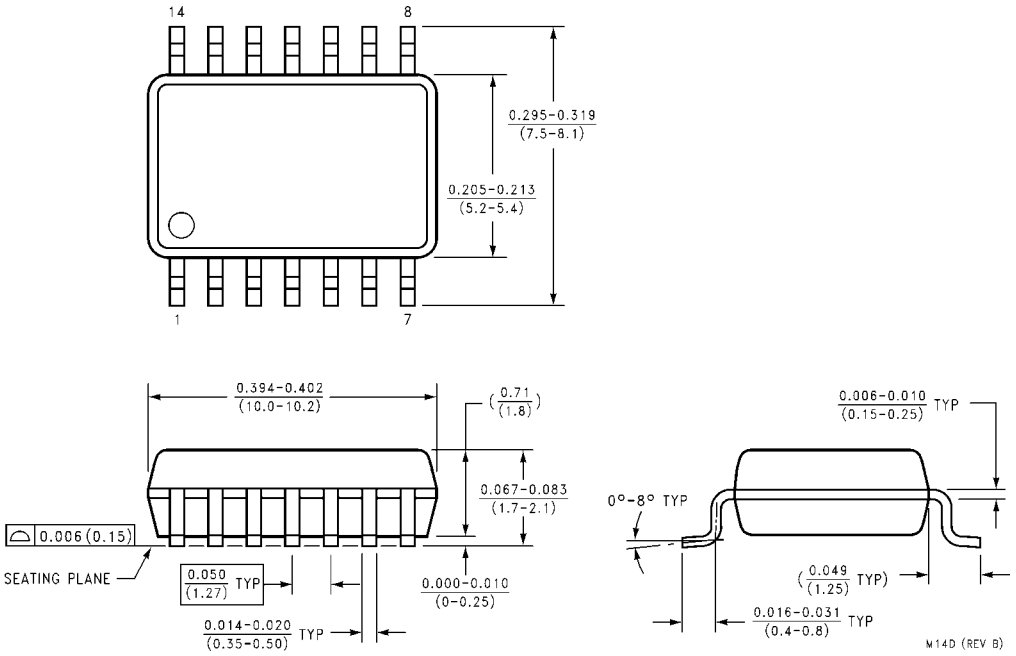
FIGURE 2. Waveforms
(Input Pulse Characteristics; f = 1MHz, $t_r = t_f$ = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted

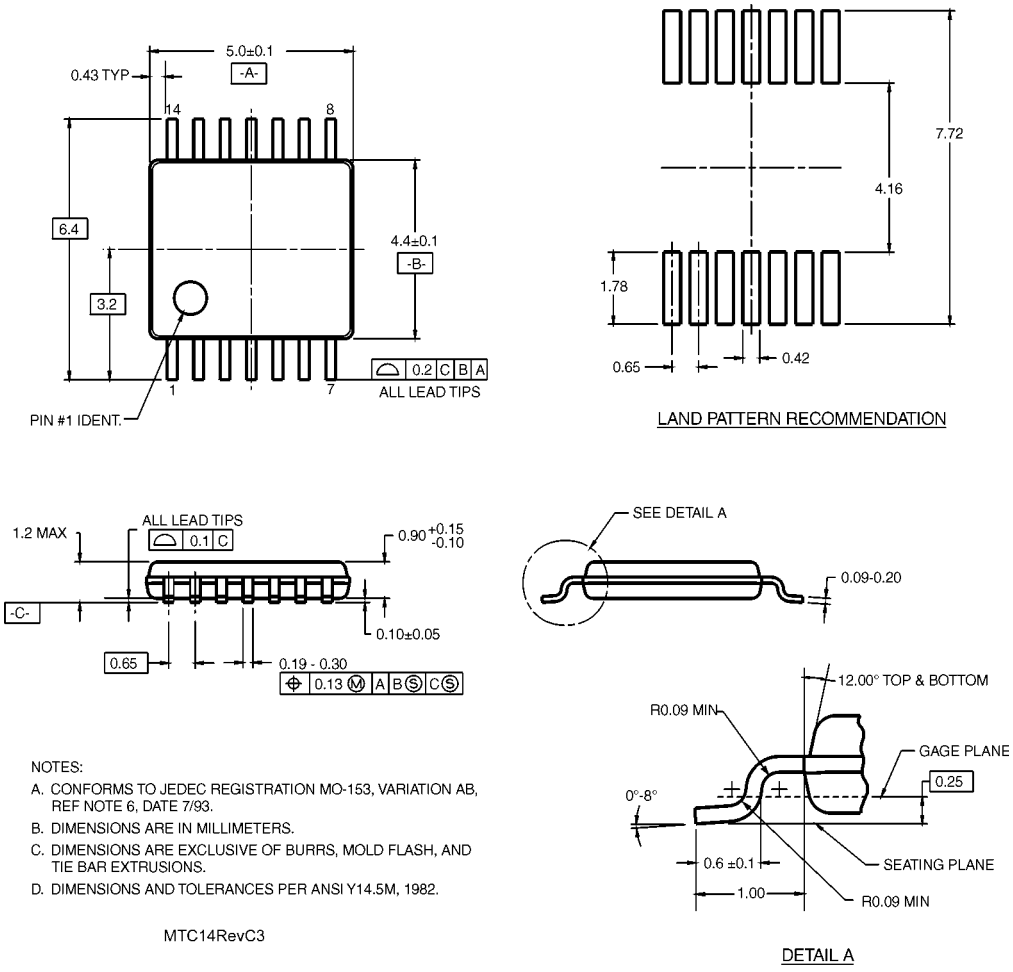


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

October 1999
Revised November 1999

74LCX07
Low Voltage Hex Buffer with Open Drain Outputs

General Description

The LCX07 contains six buffers. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The outputs of the LCX07 are open drain and can be connected to other open drain outputs to implement active HIGH wire AND or active LOW wire OR functions.

The 74LCX07 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

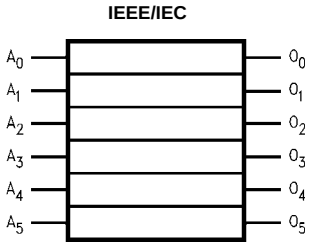
- 5V tolerant inputs
- 2.3V–5.5V V_{CC} specifications provided
- 2.9 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

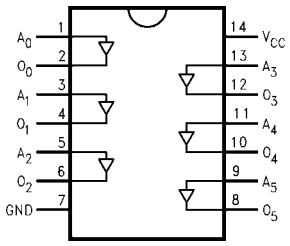
Order Number	Package Number	Package Description
74LCX07M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX07SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX07MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
O_n	Outputs

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	5.5	V
		Data Retention	1.5	5.5	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OL}	Output Current	V_{CC} = 4.5 – 5.5V		+32	mA
		V_{CC} = 3.0V – 3.6V		+24	
		V_{CC} = 2.7V – 3.0V		+12	
		V_{CC} = 2.3V – 2.7V		+8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = –40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
			4.5 – 5.5	0.7 x V_{CC}		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
			4.5 - 5.5		0.3 x V_{CC}	
V_{OL}	LOW Level Output Voltage	I_{OL} = –100 µA	2.3 – 5.5		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
		I_{OL} = 32 mA	4.5		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 5.5		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 5.5		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 5.5		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA
			4.5 – 5.5		1	mA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$								Units
		$V_{CC} = 5.0V \pm 0.5V$		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	Min	Max	
t_{PZL}	Propagation Delay Time	0.5	3.0	0.8	3.7	1.0	4.4	0.8	3.8	ns
t_{PLZ}		0.5	3.0	0.8	3.7	1.0	4.4	0.8	3.8	

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.9	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.7	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms

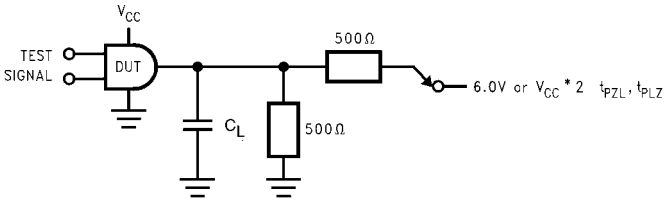
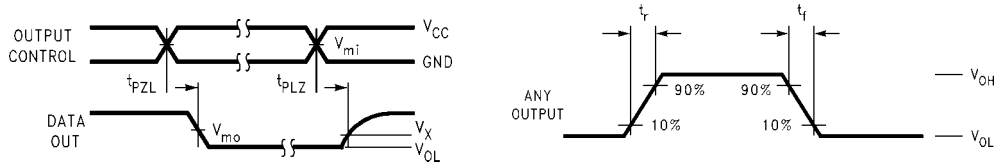


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

Test	Switch
t_{PZL}, t_{PLZ}	V_{CC} x 2 at V_{CC} = 5.0 ± 0.5V 6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V



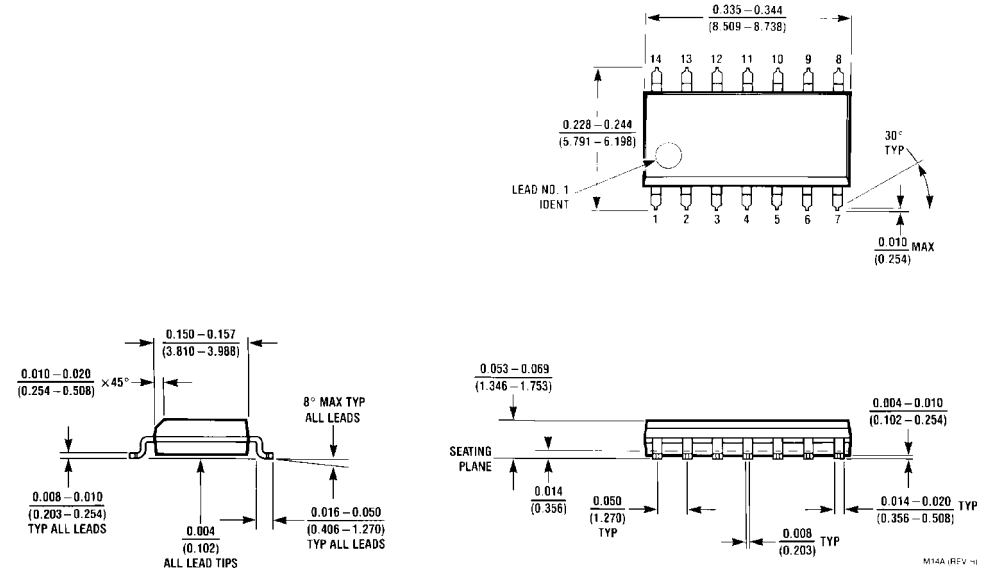
3-STATE Output Low Enable and Disable Times for Logic

t_{rise} and t_{fall}

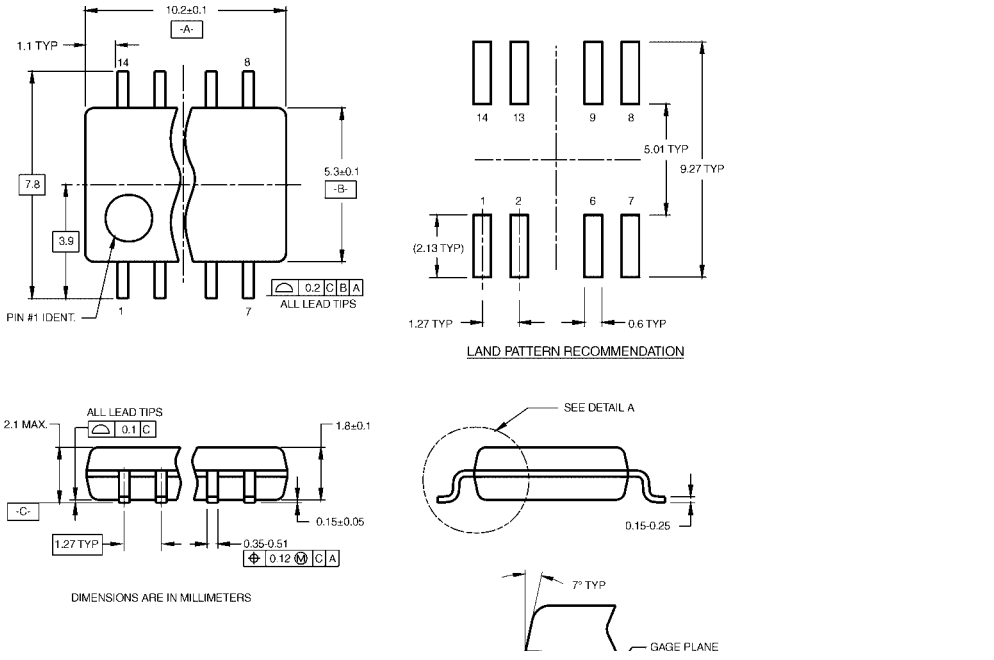
FIGURE 2. Waveforms
(Input Pulse Characteristics; f =1MHz, $t_r = t_f$ = 3ns)

Symbol	V_{CC}			
	5.0V ± 0.5V	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	V_{CC}/2	1.5V	1.5V	V_{CC}/2
V_{mo}	V_{CC}/2	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted

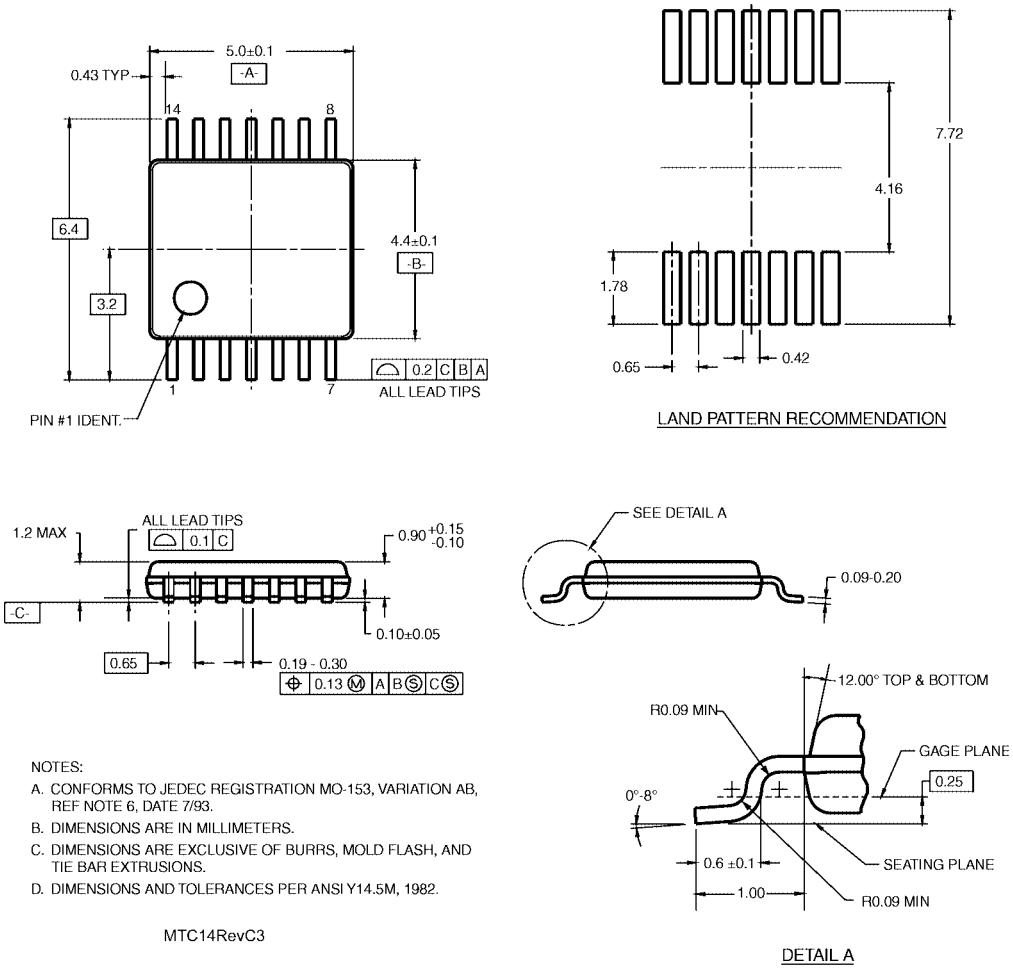


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

March 1995
Revised March 1999

74LCX08
Low Voltage Quad 2-Input AND Gate with 5V Tolerant Inputs

General Description

The LCX08 contains four 2-input AND gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LVX08 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

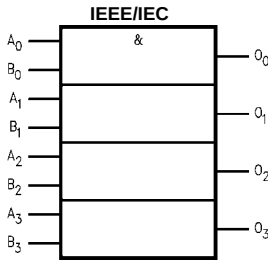
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 150V

Ordering Code:

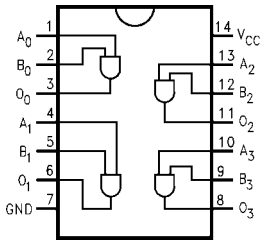
Order Number	Package Number	Package Description
74LCX08M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX08SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = –40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.3 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.2	1.5	6.6	ns
t_{PLH}		1.5	5.5	1.5	6.2	1.5	6.6	
t_{OSHL}	Output to Output Skew (Note 4)		1.0					ns
t_{OSLH}			1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

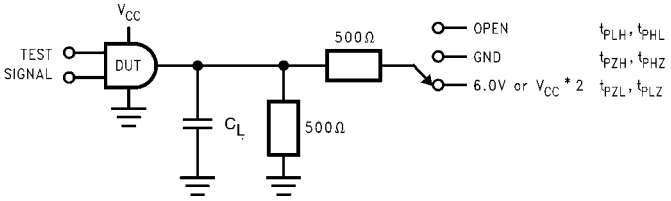
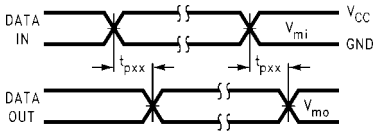
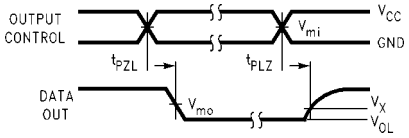


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

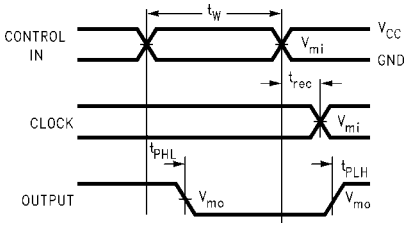
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



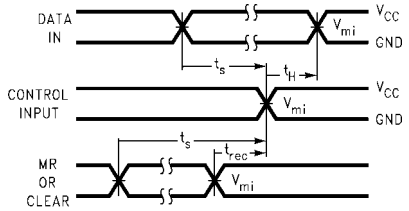
Waveform for Inverting and Non-Inverting Functions



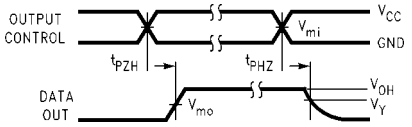
3-STATE Output Low Enable and Disable Times for Logic



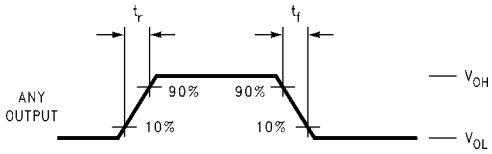
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

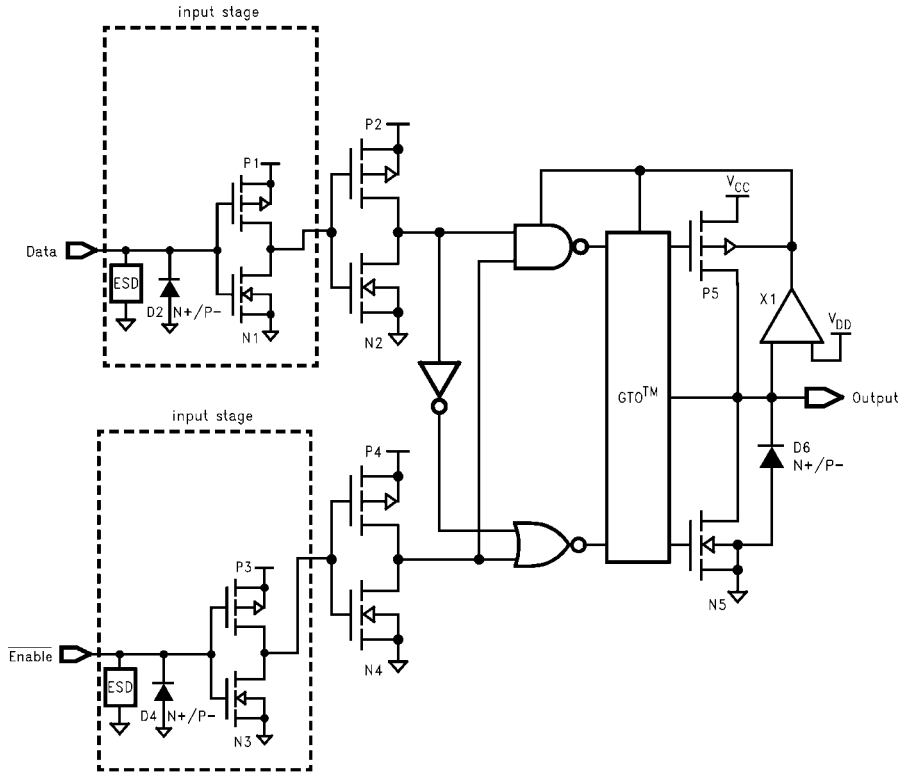


t_{rise} and t_{fall}

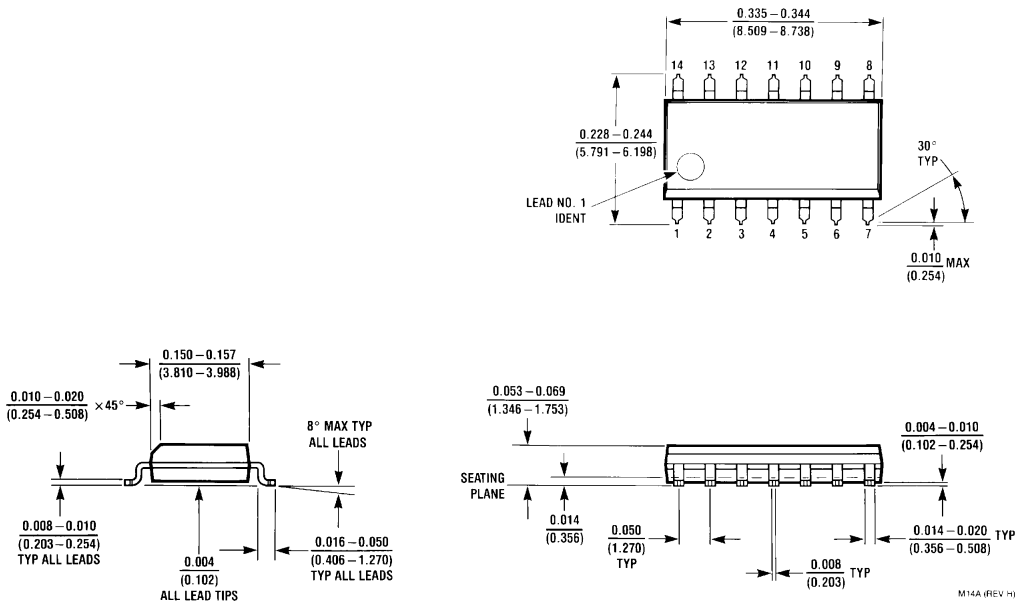
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

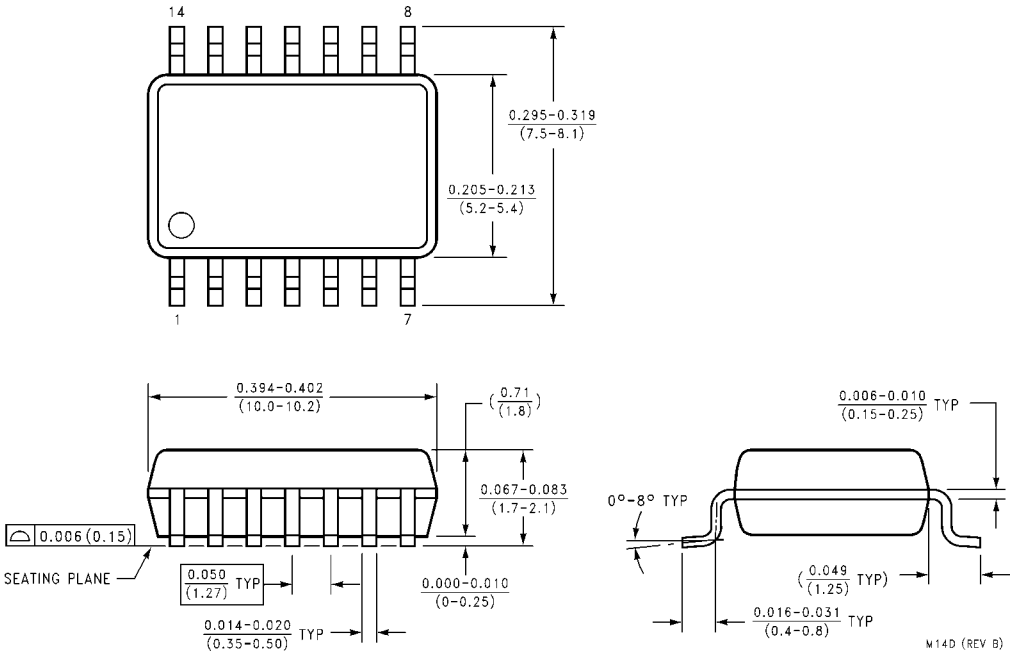
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

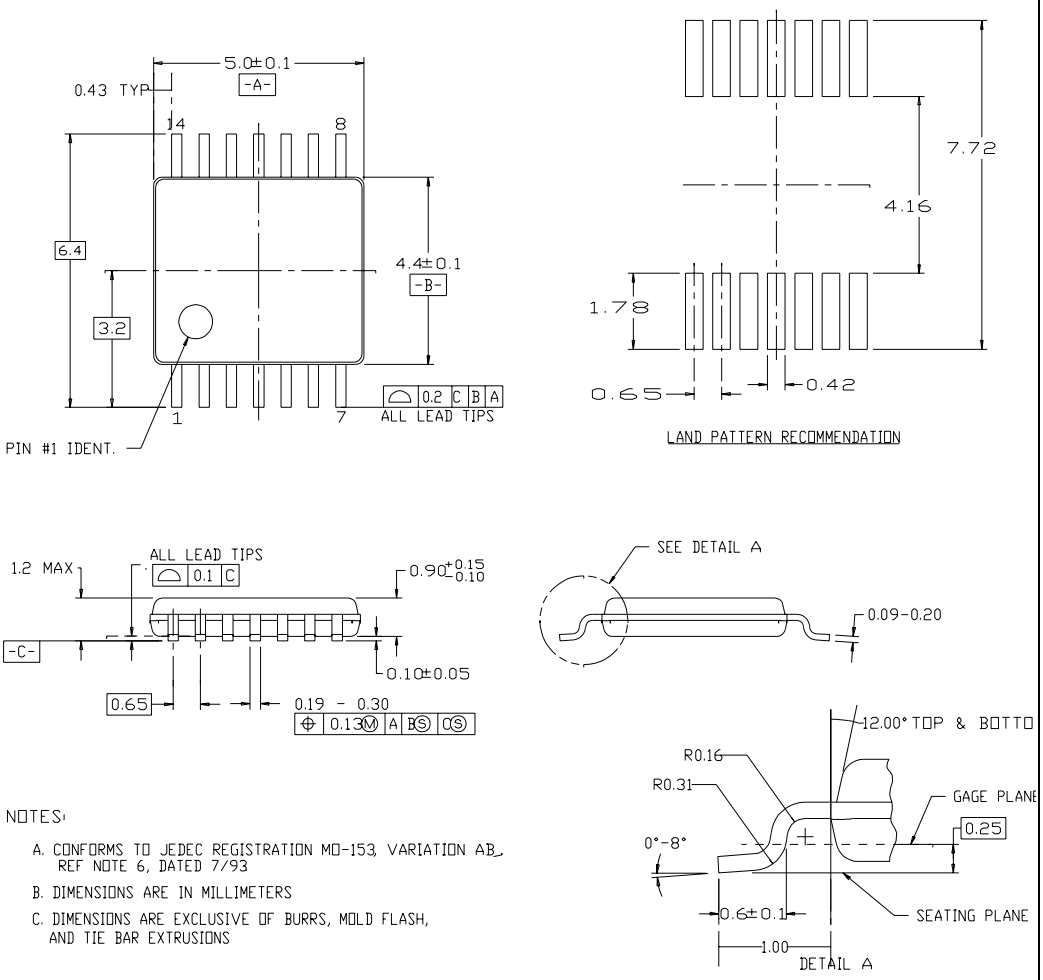


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

April 1995
Revised March 1999

74LCX11
Low Voltage Triple 3-Input AND Gate with 5V Tolerant Inputs

General Description

The LCX11 is a triple 3-input AND gate with buffered outputs. LCX devices are designed for low voltage (2.5V or 3.3V) operation with the added capability of interfacing to a 5V signal environment.

The 74LCX11 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

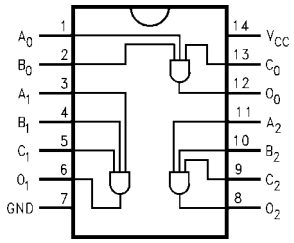
Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

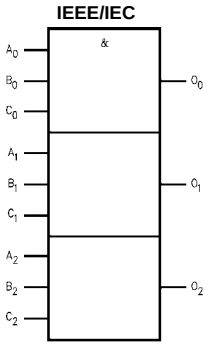
Ordering Code:

Order Number	Package Number	Package Description
74LCX11M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX11SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX11MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Connection Diagram



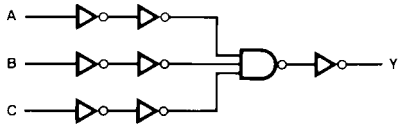
Logic Symbol



Pin Descriptions

Pin Names	Description
A_n, B_n, C_n	Inputs
O_n	Outputs

Logic Diagram



Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12mA	2.7	2.2		
		I_{OH} = −18mA	3.0	2.4		
		I_{OH} = −24mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$pF		
		Min	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PHL}		1.5	6.0	1.5	7.0	1.5	7.2	
t_{OSLH}	Output to Output Skew		1.0					ns
t_{OSHL}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L =50 pF, V_{IH} =3.3V, V_{IL} = 0V	3.3	0.8	V
		C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Peak V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	–0.8	V
		C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	7	pF
C_{OUT}	Output Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

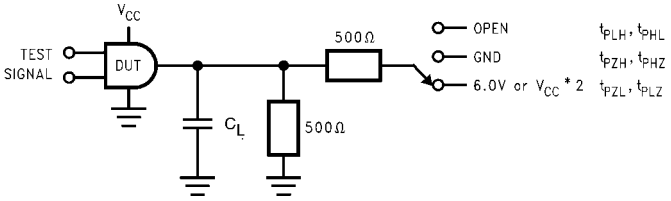
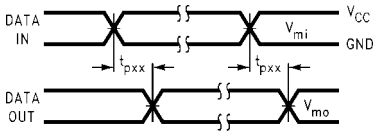
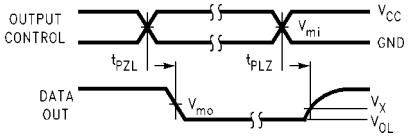


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

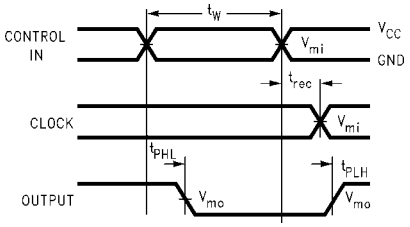
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



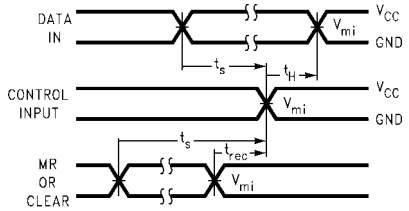
Waveform for Inverting and Non-Inverting Functions



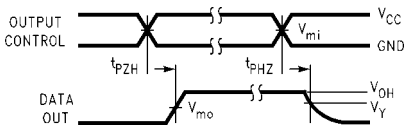
3-STATE Output Low Enable and Disable Times for Logic



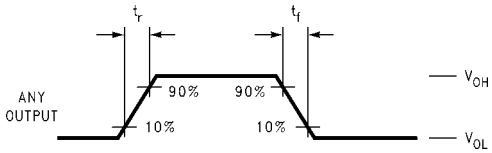
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

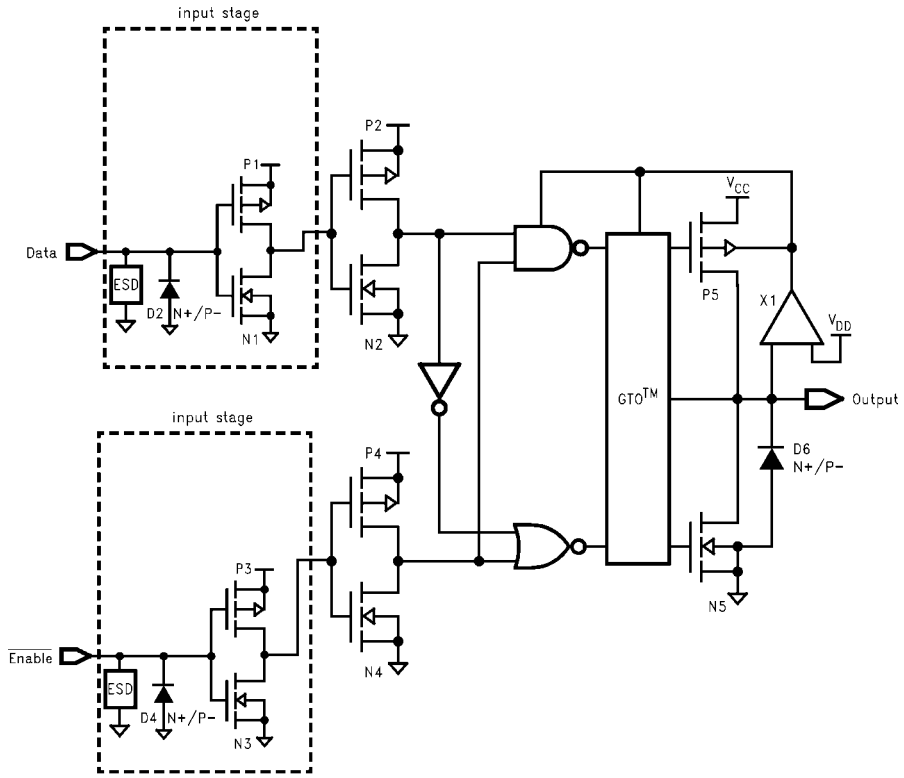


t_{rise} and t_{fall}

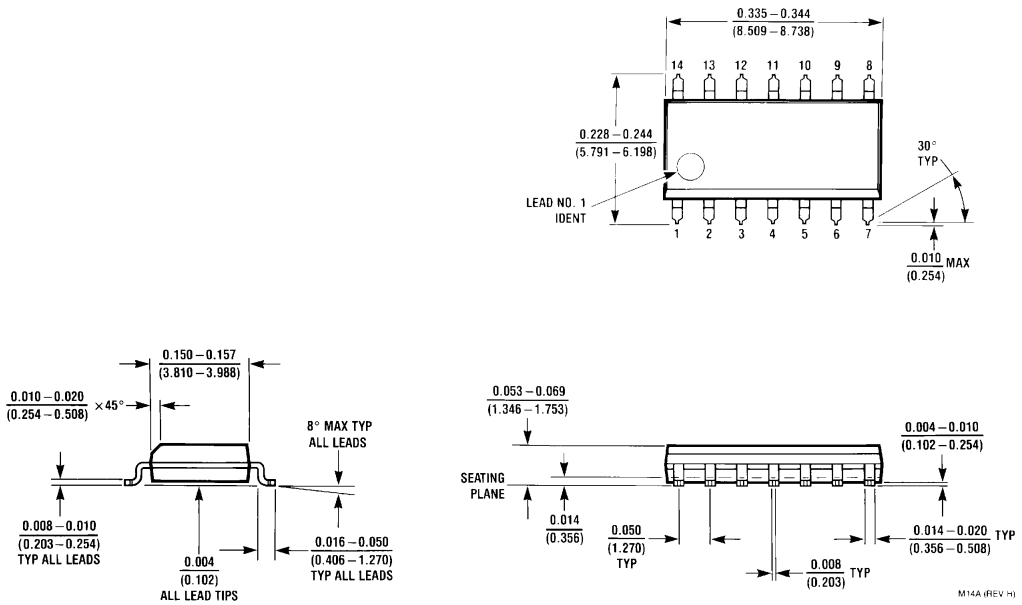
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

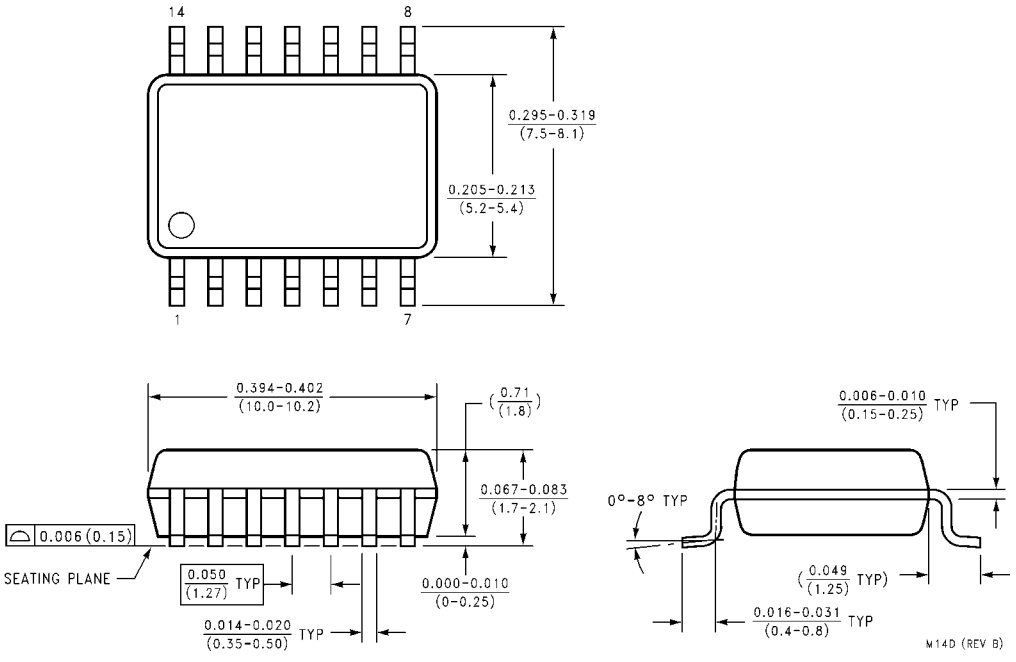
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

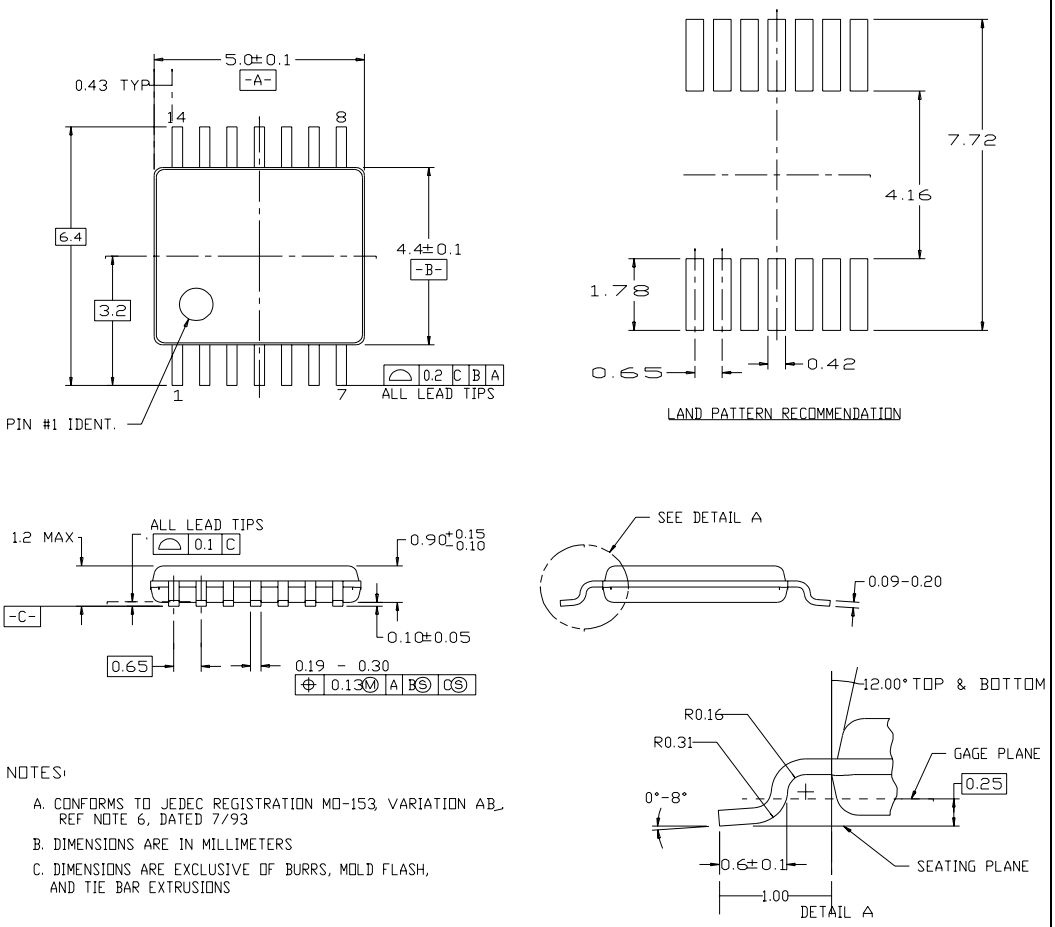


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

June 1998
Revised March 1999

74LCX112
Low Voltage Dual J-K Negative Edge-Triggered Flip-Flop with 5V Tolerant Inputs

General Description

The LCX112 is a dual J-K flip-flop. Each flip-flop has independent J, K, PRESET, CLEAR, and CLOCK inputs with Q, $\overline{Q}$ outputs. These devices are edge sensitive and change state on the negative going transition of the clock pulse. Clear and preset are independent of the clock and accomplished by a low logic level on the corresponding input. LCX devices are designed for low voltage (3.3V or 2.5) operation with the added capability of interfacing to a 5V signal environment.

The 74LCX112 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

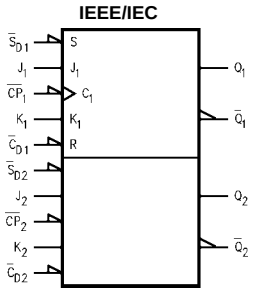
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 2000V

Ordering Code:

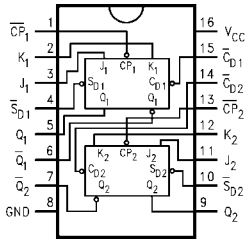
Order Number	Package Number	Package Description
74LCX112M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LCX112SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX112MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
J_1, J_2, K_1, K_2	Data Inputs
$\overline{CP}_1$, $\overline{CP}_2$	Clock Pulse Inputs (Active Falling Edge)
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs (Active LOW)
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs (Active LOW)
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs

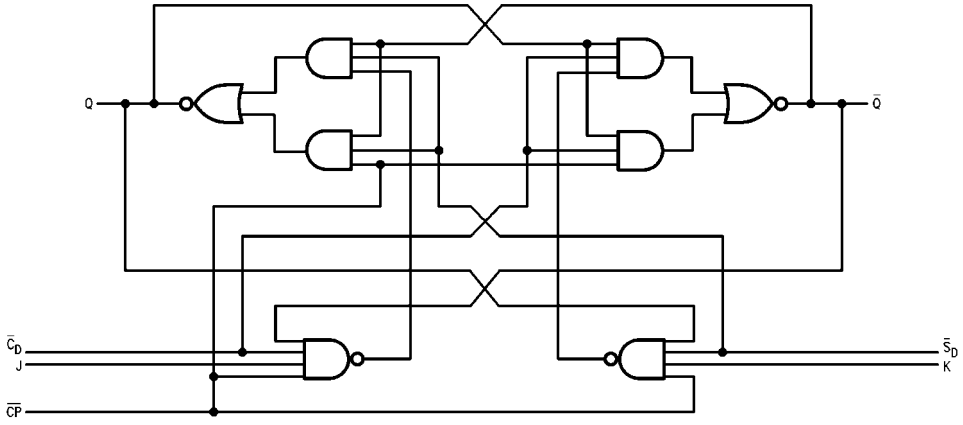
Truth Table

(Each half)

Inputs					Outputs	
$\overline{S}_D$	$\overline{C}_D$	$\overline{CP}$	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	h	h	$\overline{Q}_O$	Q_O
H	H	⌐	l	h	L	H
H	H	⌐	h	l	H	L
H	H	⌐	l	l	Q_O	$\overline{Q}_O$
H	H	H	X	X	Q_O	$\overline{Q}_O$

H(h) = HIGH Voltage Level
L(l) = LOW Voltage Level
X = Immaterial
⌐ = HIGH-to-LOW Clock Transition
$Q_O(\overline{Q}_O)$ = Before HIGH-to-LOW Transition of Clock
Lower case letters indicate the state of the referenced input or output one setup time prior to the HIGH-to-LOW clock transition.

Logic Diagram



Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supple Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to 150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum rating must be observed.

Note 3: Unused Inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = 40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100µA	2.3 – 3.6	V_{CC} - 0.2	0.7	V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.6	V
		I_{OL} = 8mA	2.3		0.2	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ I_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameters	$T_A = 40°C$ to $85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		C_L=50 pF		C_L = 50 pF		C_L=30 pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150		150		150		MHz
t_{PHL}	Propagation Delay	1.5	7.5	1.5	8.0	1.5	9.0	ns
t_{PLH}	$\overline{CP}_n$ to Q_n or $\overline{Q}_n$	1.5	7.5	1.5	8.0	1.5	9.0	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	1.5	7.0	1.7	8.0	1.5	8.4	
t_S	Setup Time	2.5		2.5		4.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width $\overline{CP}$	3.3		3.3		4.0		ns
t_W	Pulse Width ($\overline{C}_D$, $\overline{S}_D$)	3.3		3.3		4.0		ns
t_{REC}	Recovery Time	2.0		2.5		4.5		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}), or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	0.8	V
		C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	–0.8	V
		C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	7	pF
C_{OUT}	Output Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

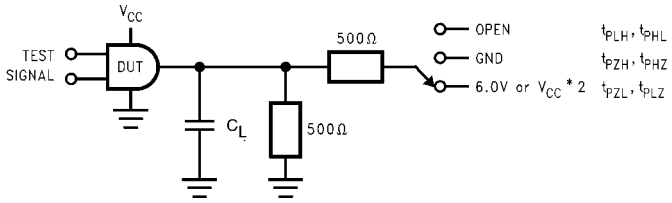
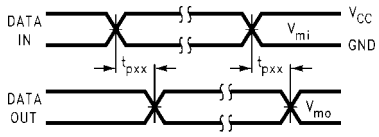
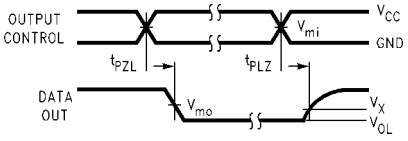


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

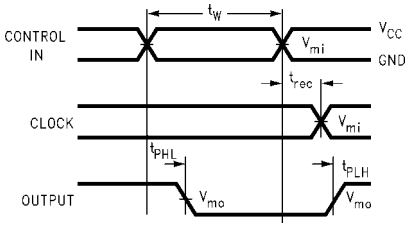
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



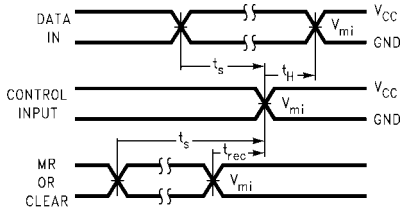
Waveform for Inverting and Non-Inverting Functions



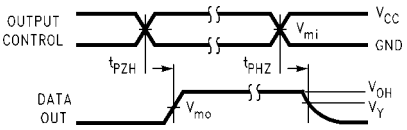
3-STATE Output Low Enable and Disable Times for Logic



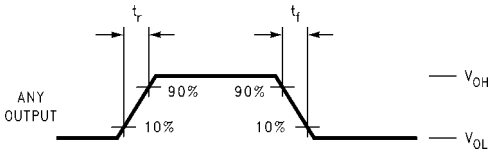
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

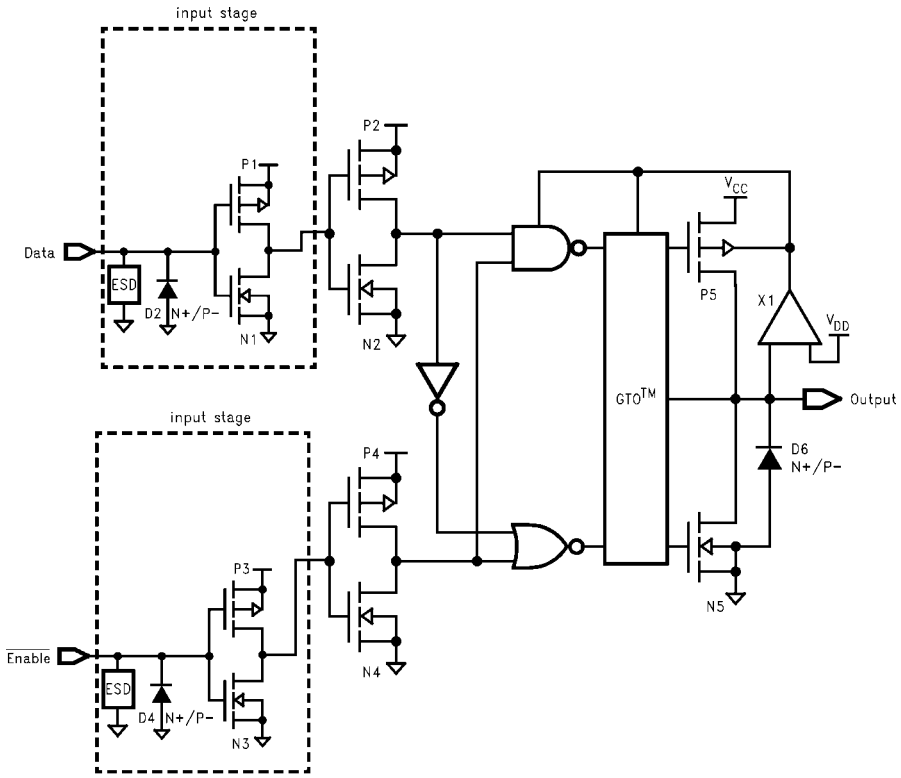


t_{rise} and t_{fall}

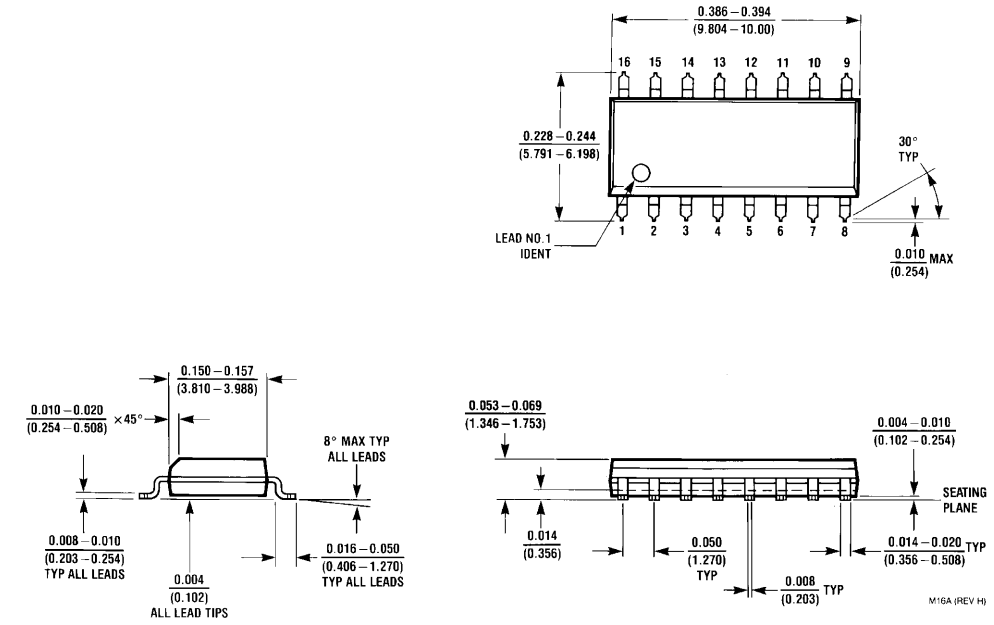
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

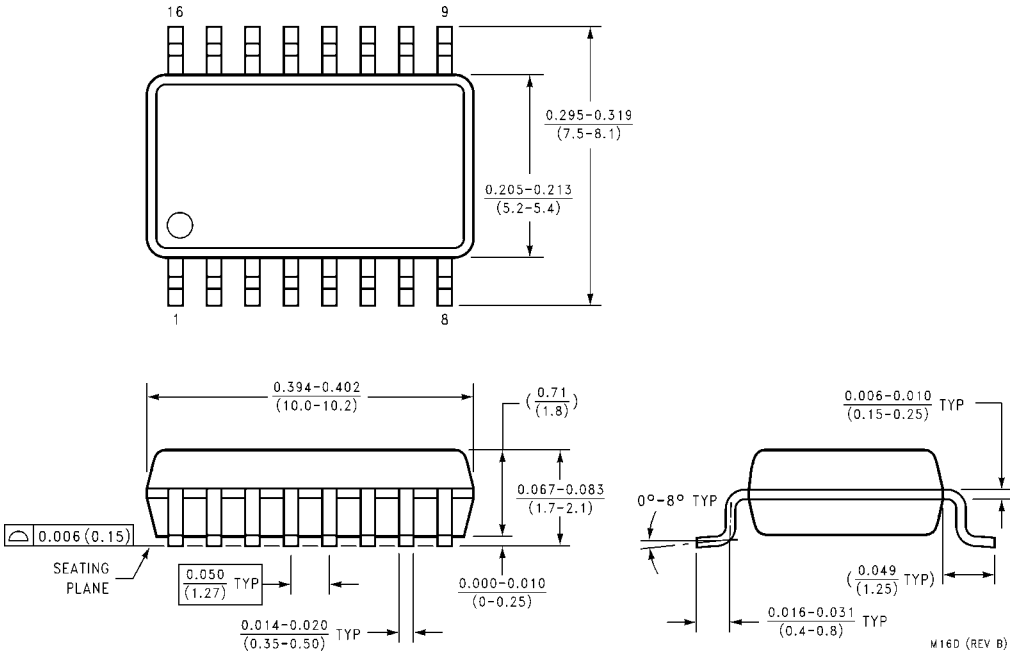
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

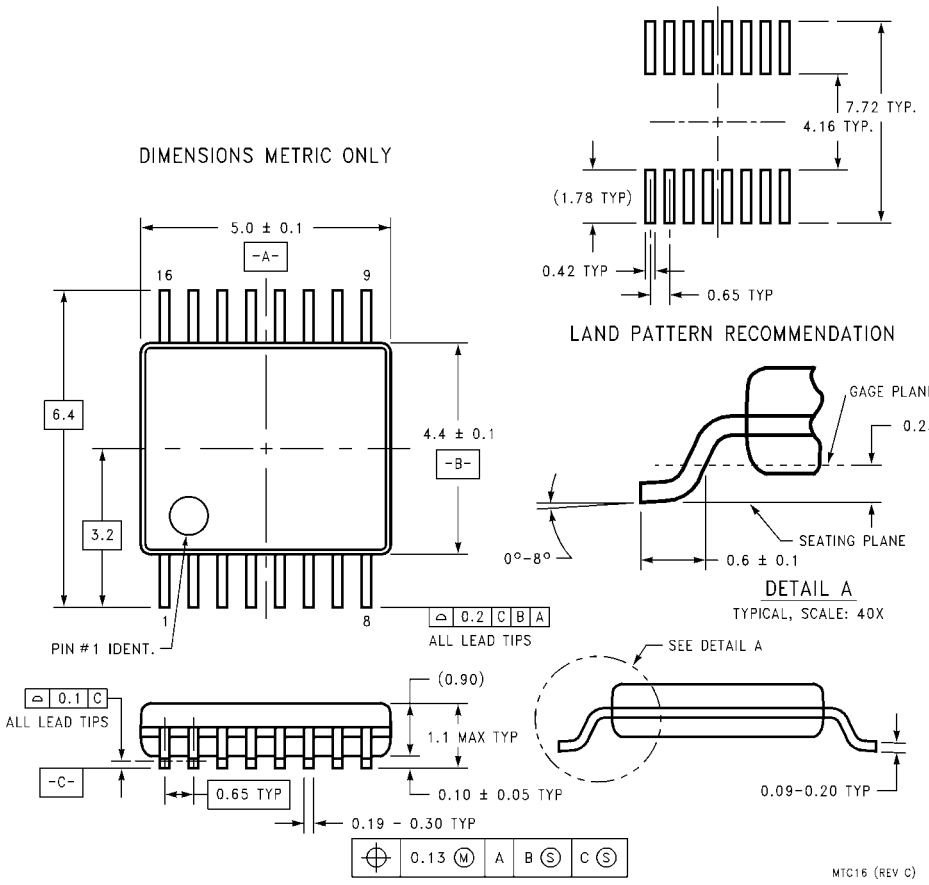


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX125
Low Voltage Quad Buffer with 5V Tolerant Inputs and Outputs

General Description

The LCX125 contains four independent non-inverting buffers with 3-STATE outputs. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX125 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 100V

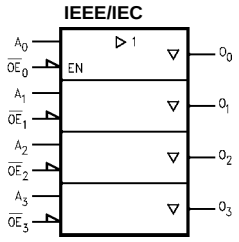
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

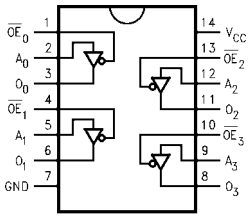
Order Number	Package Number	Package Description
74LCX125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{OE}_n$	Output Enable Inputs
O_n	Outputs

Truth Table

Inputs		Output
$\overline{OE}_n$	A_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to +7.0	Output in 3-STATE	V
		–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = –40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.0	1.5	6.5	1.5	7.2	ns
t_{PLH}		1.5	6.0	1.5	6.5	1.5	7.2	
t_{PZL}	Output Enable Time	1.5	7.0	1.5	8.0	1.5	9.1	ns
t_{PZH}		1.5	7.0	1.5	8.0	1.5	9.1	
t_{PLZ}	Output Disable Time	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PHZ}		1.5	6.0	1.5	7.0	1.5	7.2	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

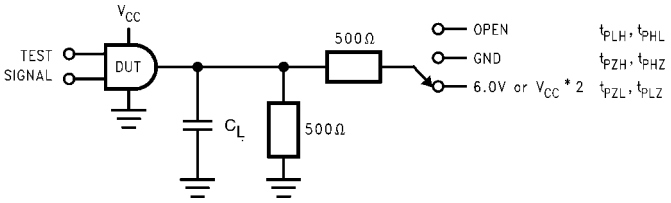
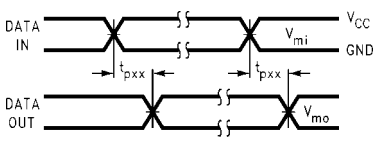
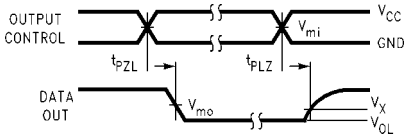


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

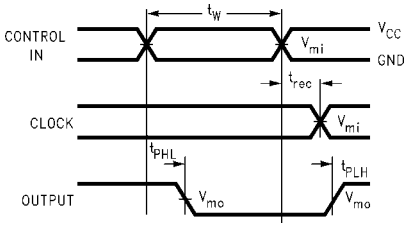
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



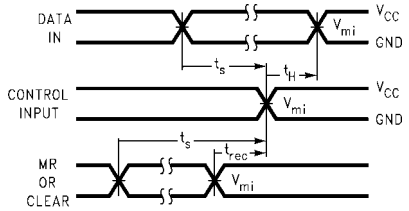
Waveform for Inverting and Non-Inverting Functions



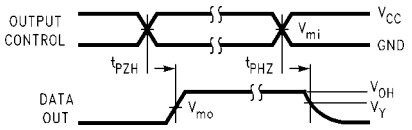
3-STATE Output Low Enable and Disable Times for Logic



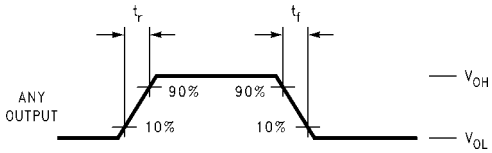
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

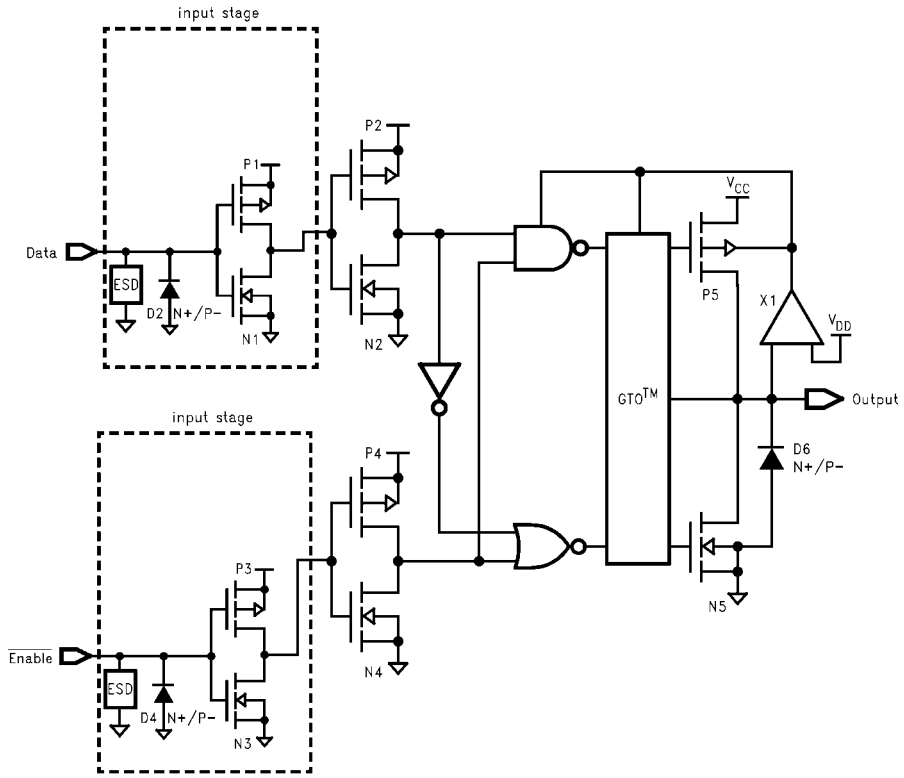


t_{rise} and t_{fall}

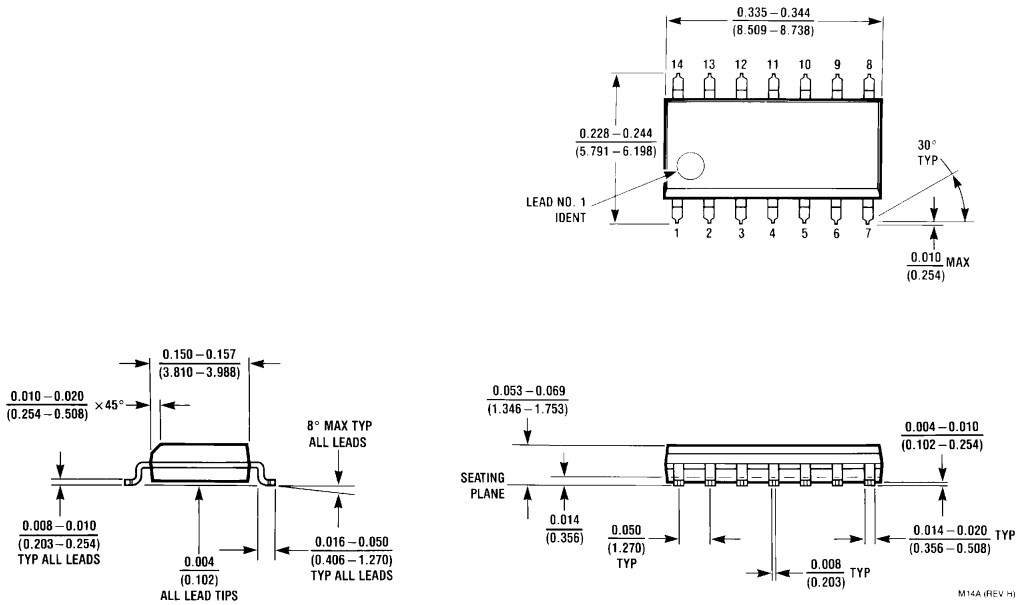
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

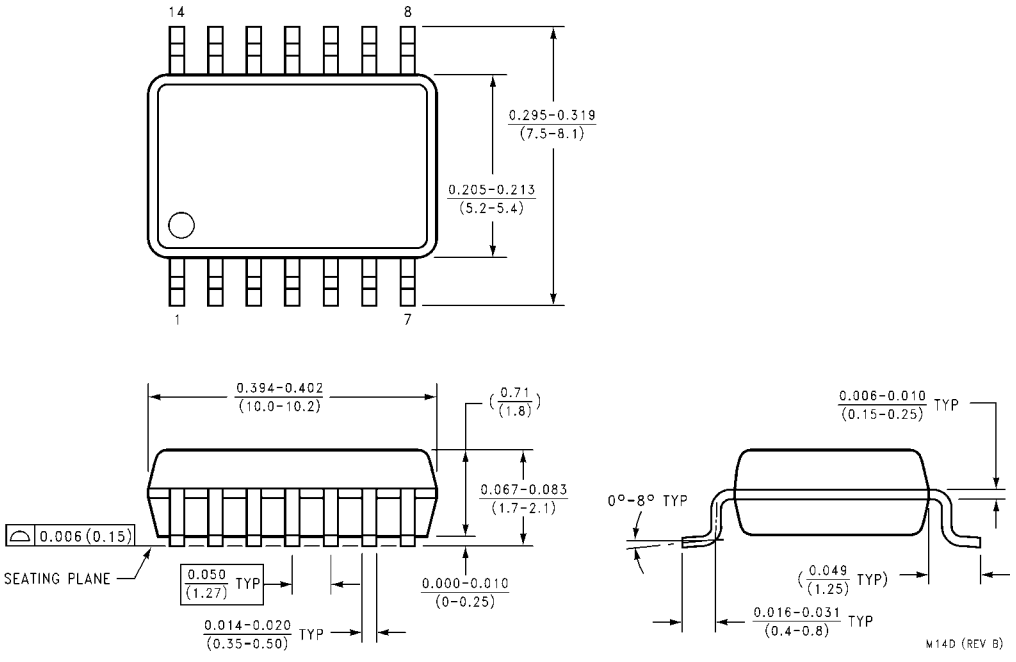
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

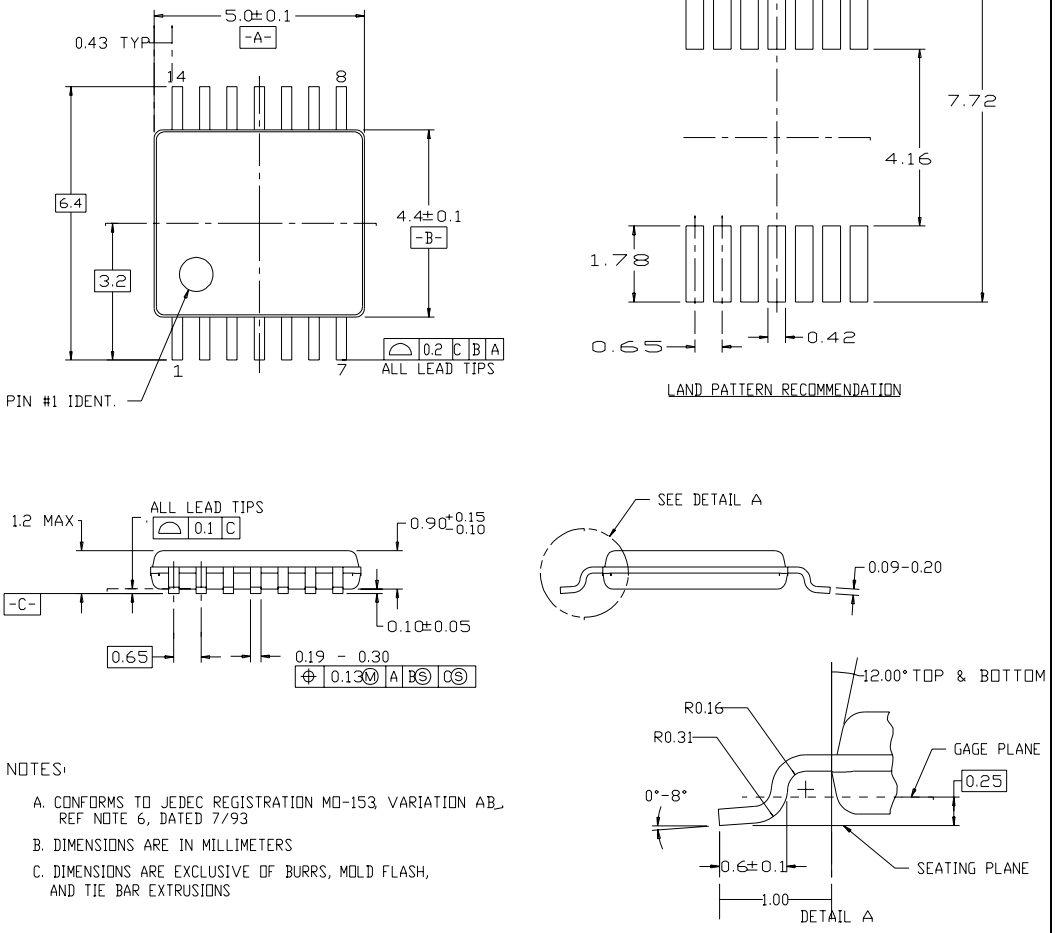


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised March 1999

74LCX138
Low Voltage 1-of-8 Decoder/Demultiplexer with 5V Tolerant Inputs

General Description

The LCX138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three LCX138 devices or a 1-of-32 decoder using four LCX138 devices and one inverter.

The 74LCX138 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

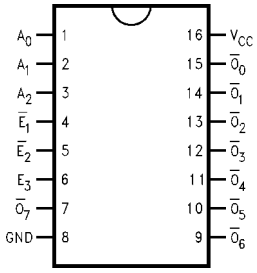
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description
74LCX138M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LCX138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX138MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_2	Address Inputs
$\overline{E}_1$–$\overline{E}_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0$–$\overline{O}_7$	Outputs

Functional Description

The LCX138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A_0, A_1, A_2) and, when enabled, provides eight mutually exclusive active-LOW outputs ($\overline{O}_0$–$\overline{O}_7$). The LCX138 features three Enable inputs, two active-LOW ($\overline{E}_1$, $\overline{E}_2$) and one active-HIGH (E_3).

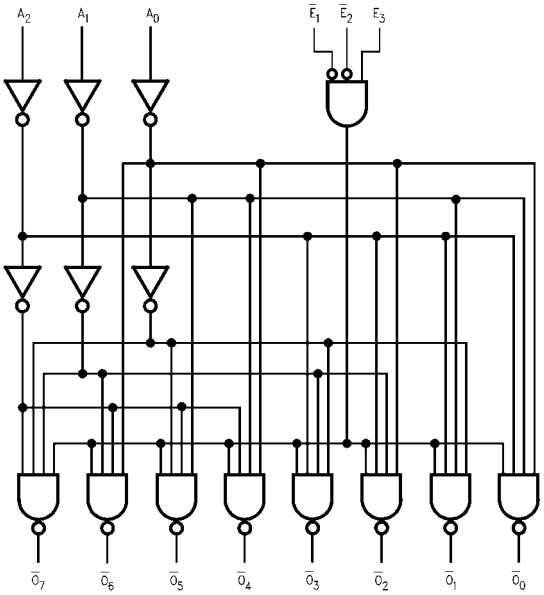
All outputs will be HIGH unless $\overline{E}_1$ and $\overline{E}_2$ are LOW and E_3 is HIGH. The LCX138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active-HIGH or active-LOW state.

Truth Table

Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = –40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50pF$		$C_L = 50pF$		$C_L = 30pF$		
		Min	Max	Min	Max	Min	Max	
$t_{PHL}t_{PLH}$	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
	An to $\overline{Qn}$	1.5	6.0	1.5	7.0	1.5	7.2	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	8.4	ns
t_{PLH}	E3 to $\overline{Qn}$	1.5	6.5	1.5	7.5	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PLH}	$\overline{E1}$ or $\overline{E2}$ to $\overline{Qn}$	1.5	6.0	1.5	7.0	1.5	7.2	
t_{OSHL}	Output to Output Skew (Note 4)		1.0					ns
t_{OSLH}			1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

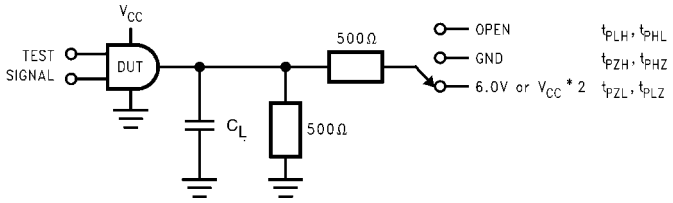
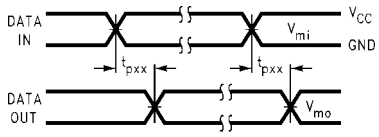
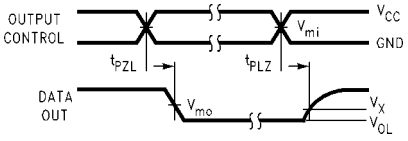


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

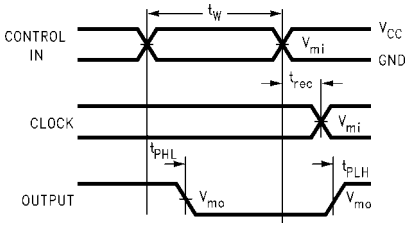
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



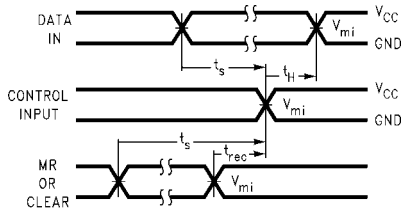
Waveform for Inverting and Non-Inverting Functions



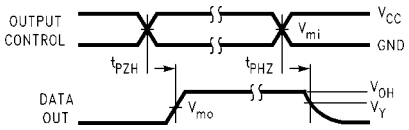
3-STATE Output Low Enable and Disable Times for Logic



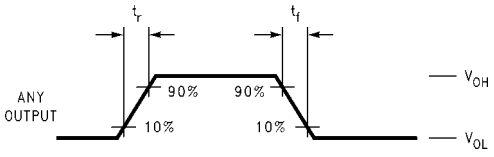
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable Times for Logic

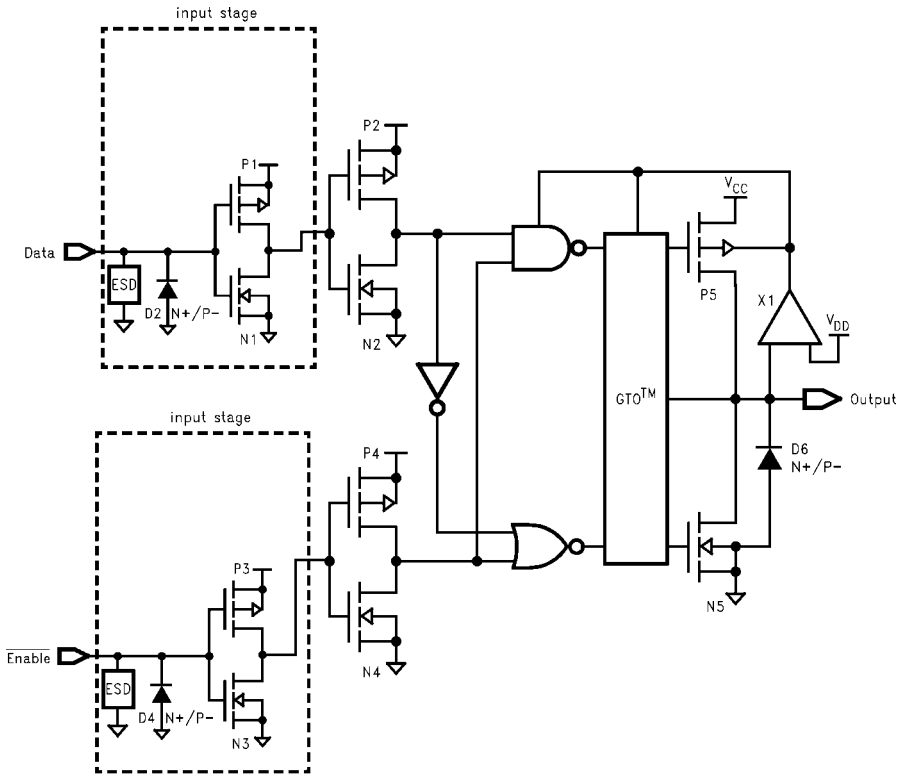


t_{rise} and t_{fall}

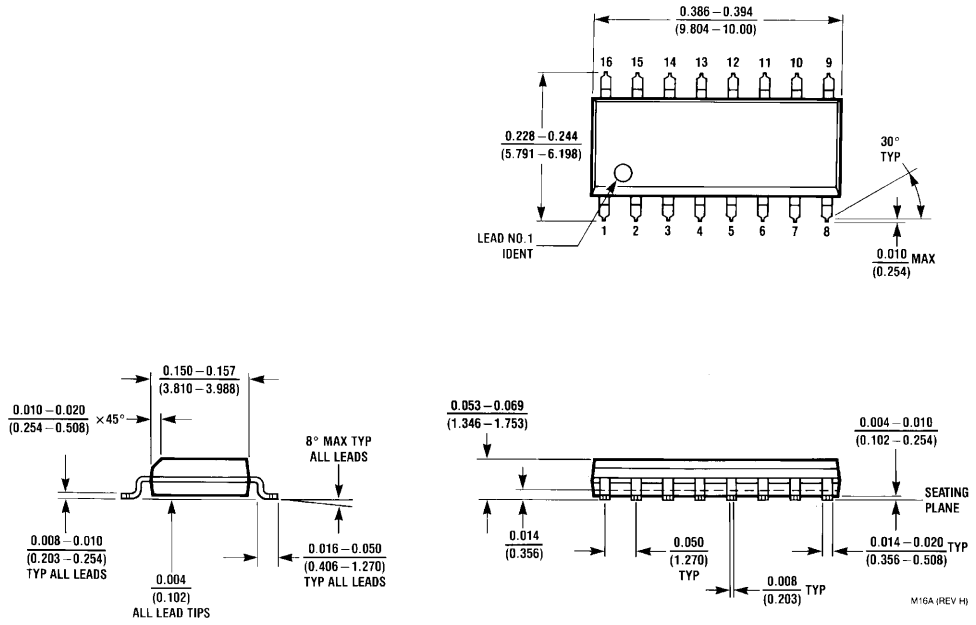
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

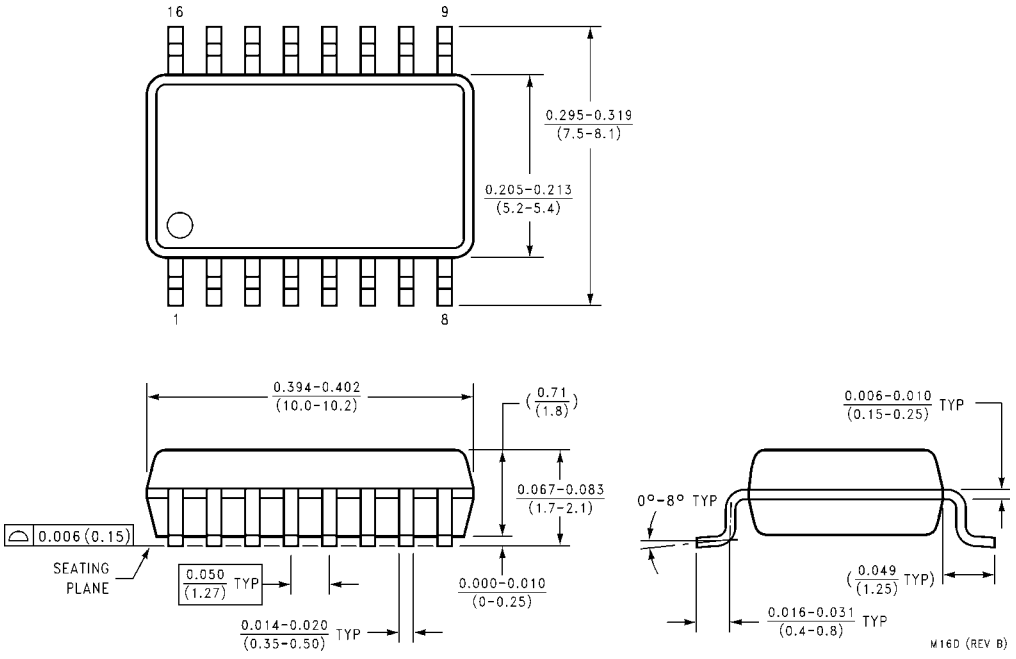
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

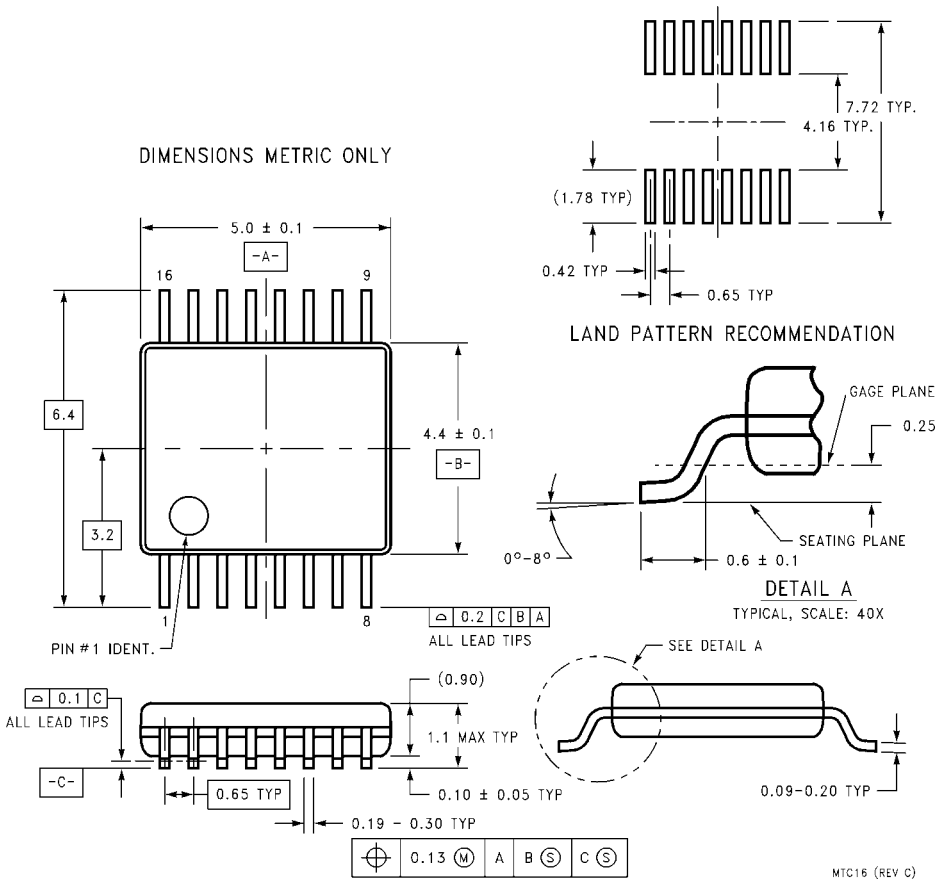


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised March 1999

74LCX14
Low Voltage Hex Inverter with 5V Tolerant Schmitt Trigger Inputs

General Description

The LCX14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LCX14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

The inputs tolerate voltages up to 7V allowing the interface of 5V, 3V and 2.5V systems.

The 74LCX14 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

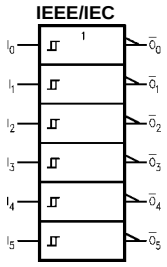
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Machine model > 2000V
  - Human model > 200V

Ordering Code:

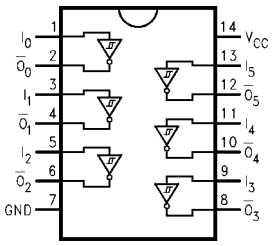
Order Number	Package Number	Package Description
74LCX14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
I_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

Input	Output
A	$\overline{\mathbf{O}}$
L	H
H	L

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = –40°C to +85°C Min	T_A = –40°C to +85°C Max	Units
V_{t+}	Positive Input Threshold		2.5	0.9	1.7	V
			3.0	1.2	2.2	
V_{t-}	Negative Input Threshold		2.5	0.4	1.1	V
			3.0	0.6	1.5	
V_H	Hysteresis		2.5	0.3	1.0	V
			3.0	0.4	1.2	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay Time	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}		1.5	6.5	1.5	7.5	1.5	7.8	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	−0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

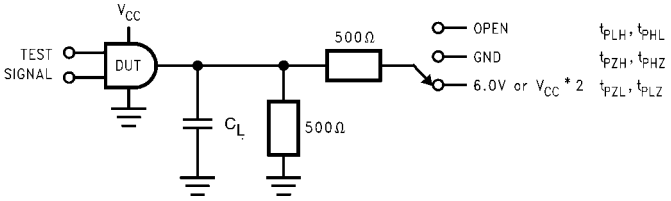
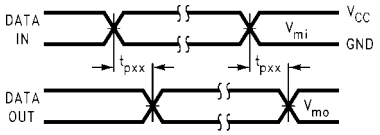
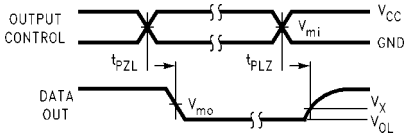


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

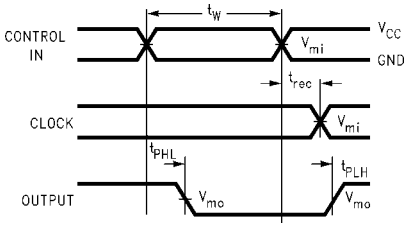
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



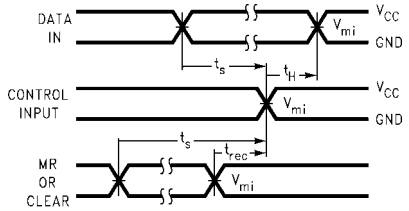
Waveform for Inverting and Non-Inverting Functions



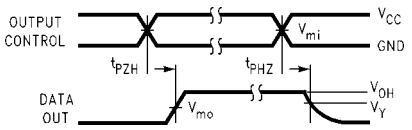
3-STATE Output Low Enable and Disable Times for Logic



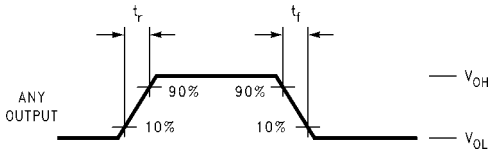
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

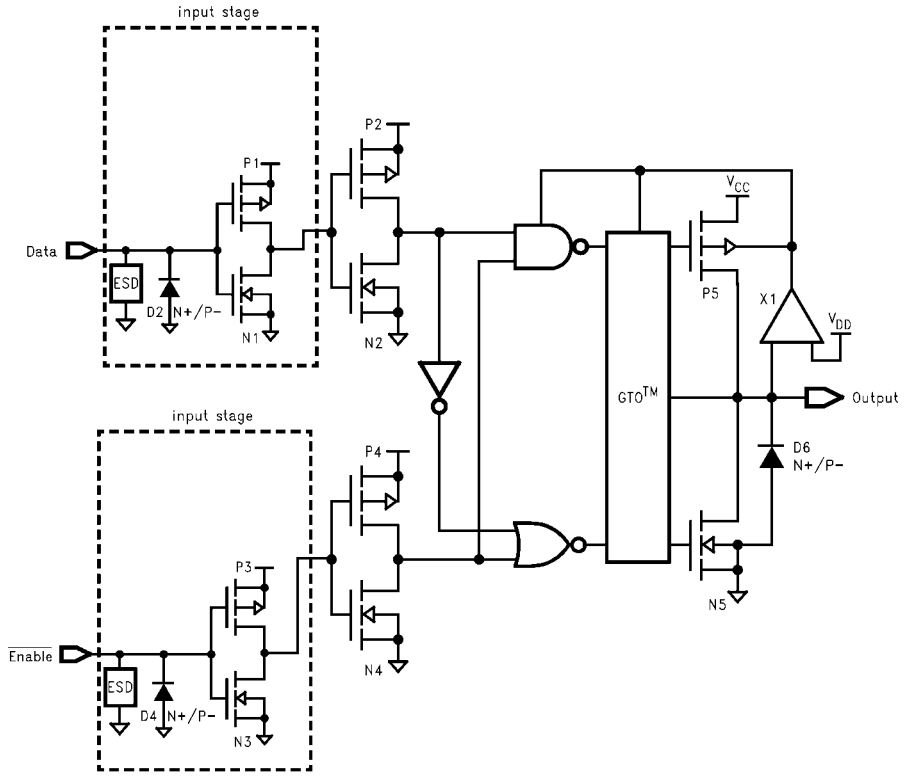


t_{rise} and t_{fall}

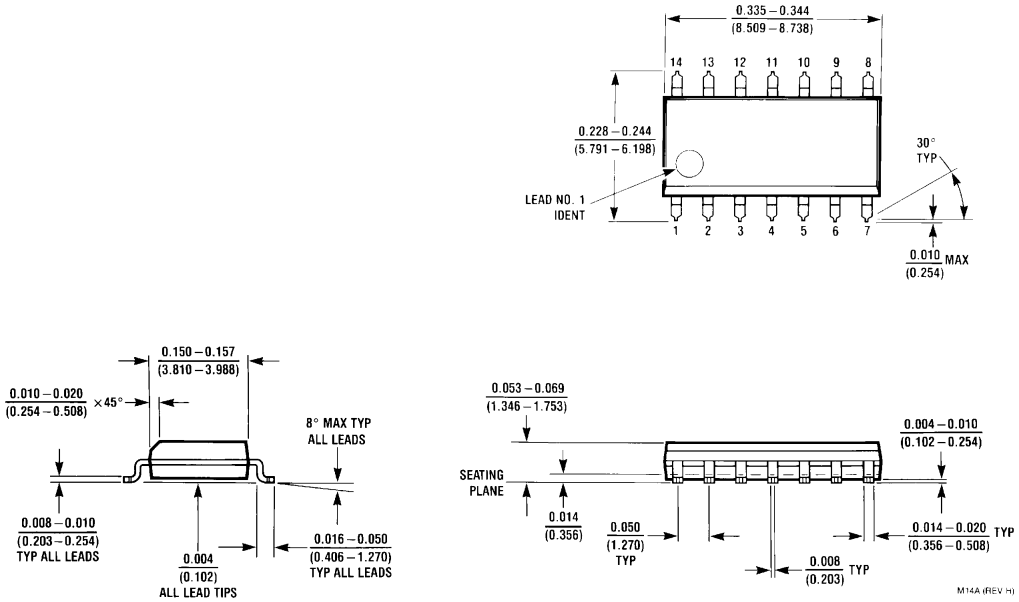
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

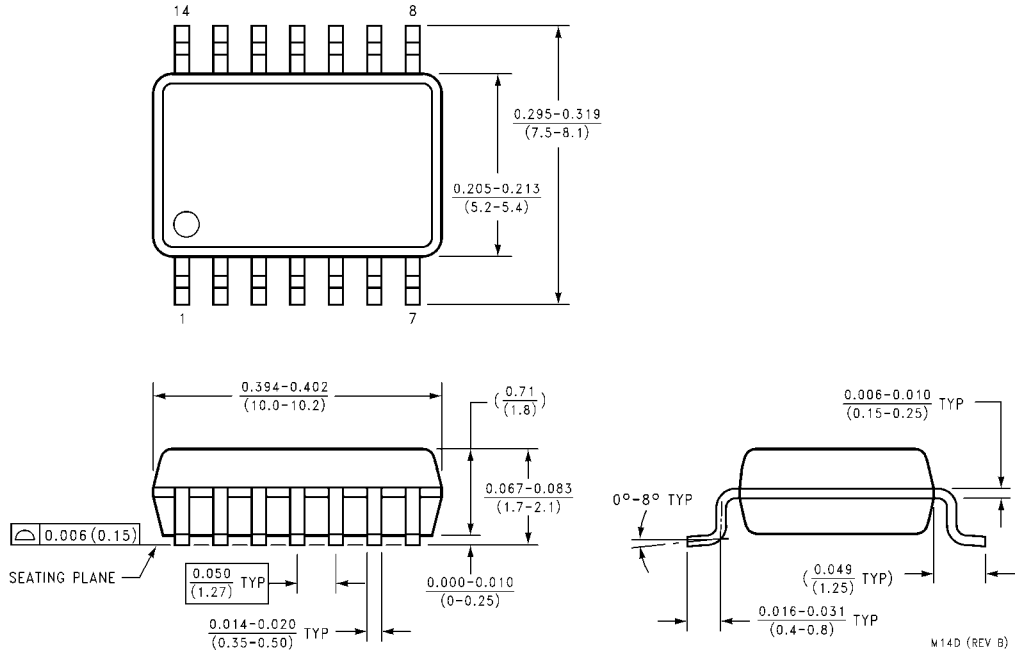
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

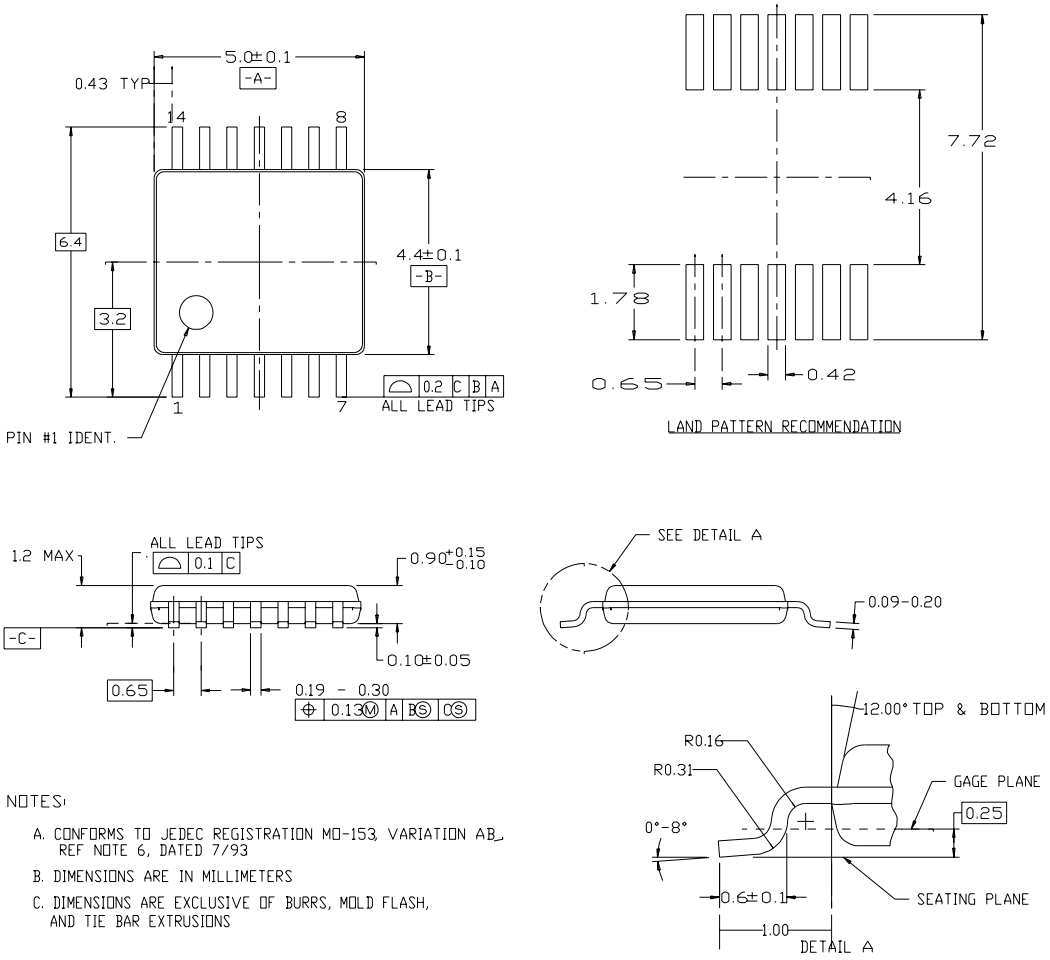


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

May 1995
Revised March 1999

74LCX157
Low Voltage Quad 2-Input Multiplexer with 5V Tolerant Inputs

General Description

The LCX157 is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (noninverted) form. The LCX157 can also be used as a function generator.

The 74LCX157 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

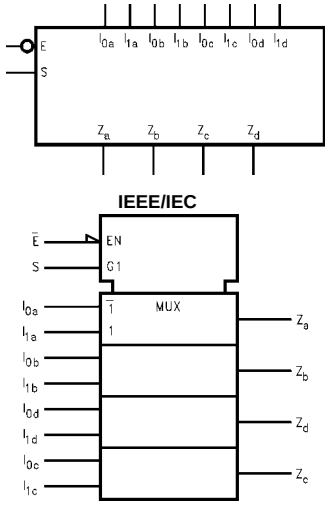
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.8 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

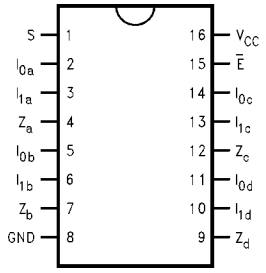
Order Number	Package Number	Package Description
74LCX157M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LCX157SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX157MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{E}$	Enable Input
S	Select Input
Z_a–Z_d	Outputs

Functional Description

The LCX157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\overline{E}$) is active-LOW. When $\overline{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The LCX157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$Z_a = \overline{E} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$

$Z_b = \overline{E} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$

$Z_c = \overline{E} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$

$Z_d = \overline{E} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$

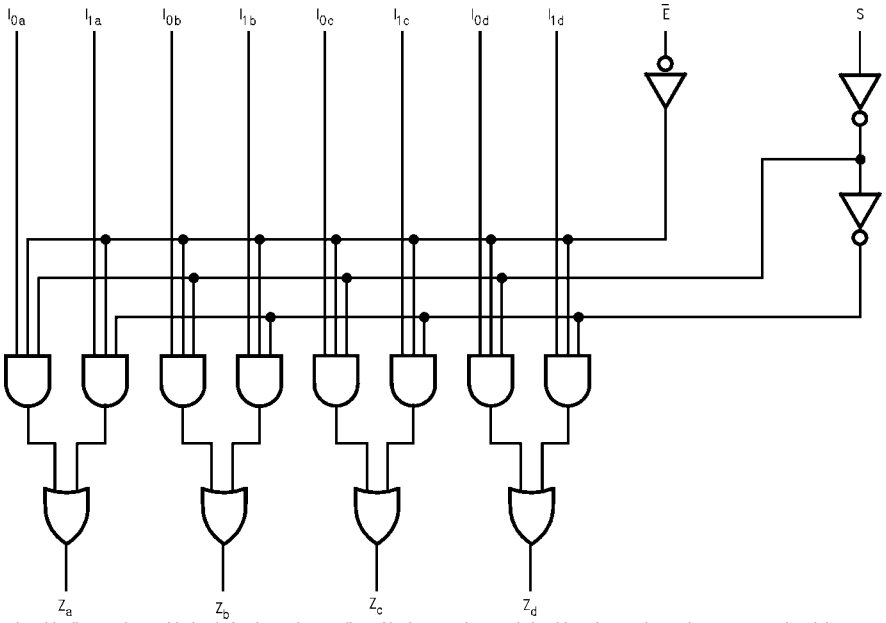
A common use of the LCX157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The LCX157 can generate any four of the sixteen different functions of two variables with one variable common. This is useful for implementing gating functions.

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OH} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 − 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 − 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.3 − 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	$S \rightarrow Z_n$	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	$\overline{E} \rightarrow Z_n$	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	5.8	1.5	6.3	1.5	7.0	ns
t_{PLH}	$I_n \rightarrow Z_n$	1.5	5.8	1.5	6.3	1.5	7.0	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		CL= 30 pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		CL= 30 pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	-0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

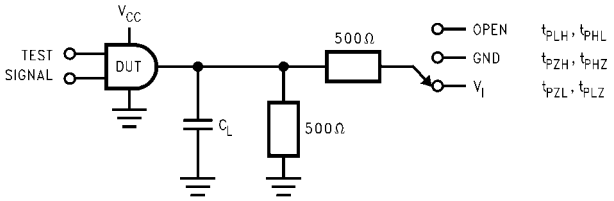
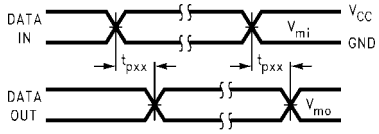
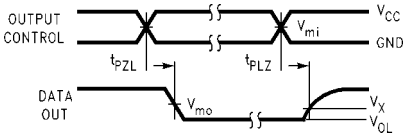


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

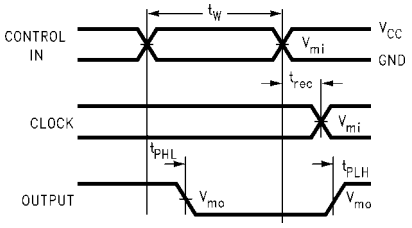
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH}, t_{PHZ}	GND



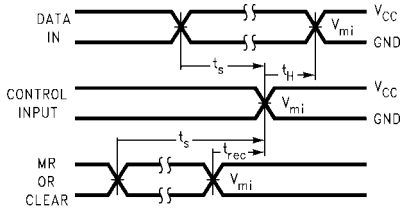
Waveform for Inverting and Non-Inverting Functions



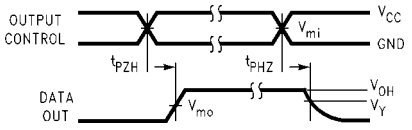
3-STATE Output Low Enable and Disable Times for Logic



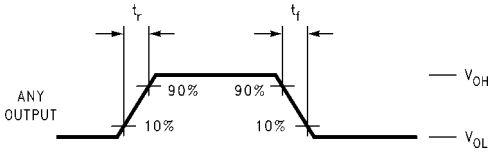
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output High Enable and Disable Times for Logic

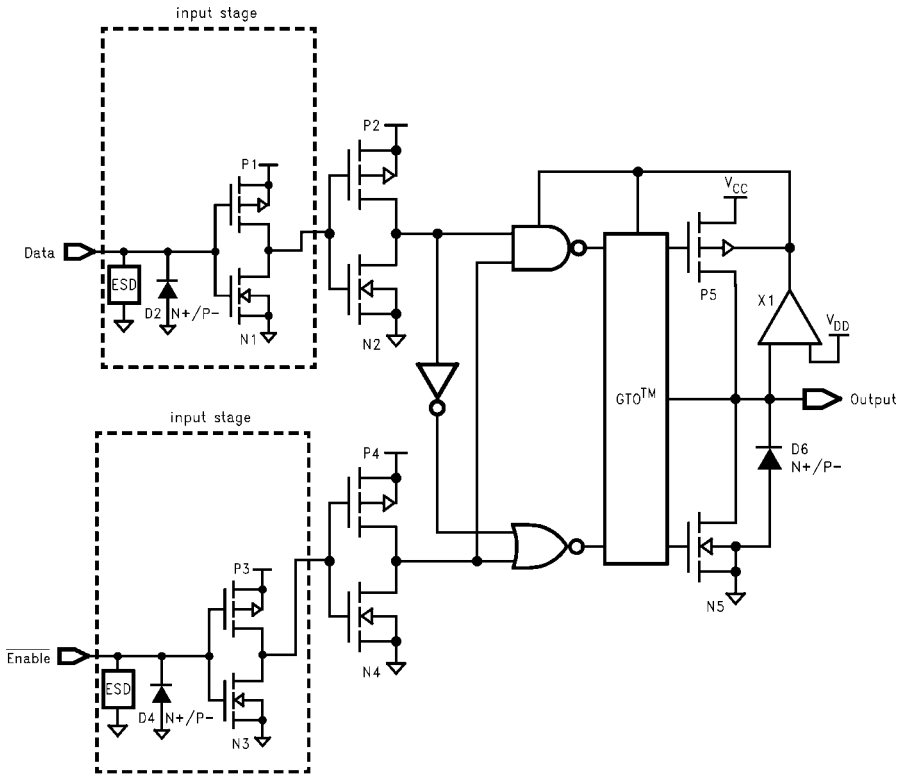


t_{rise} and t_{fall}

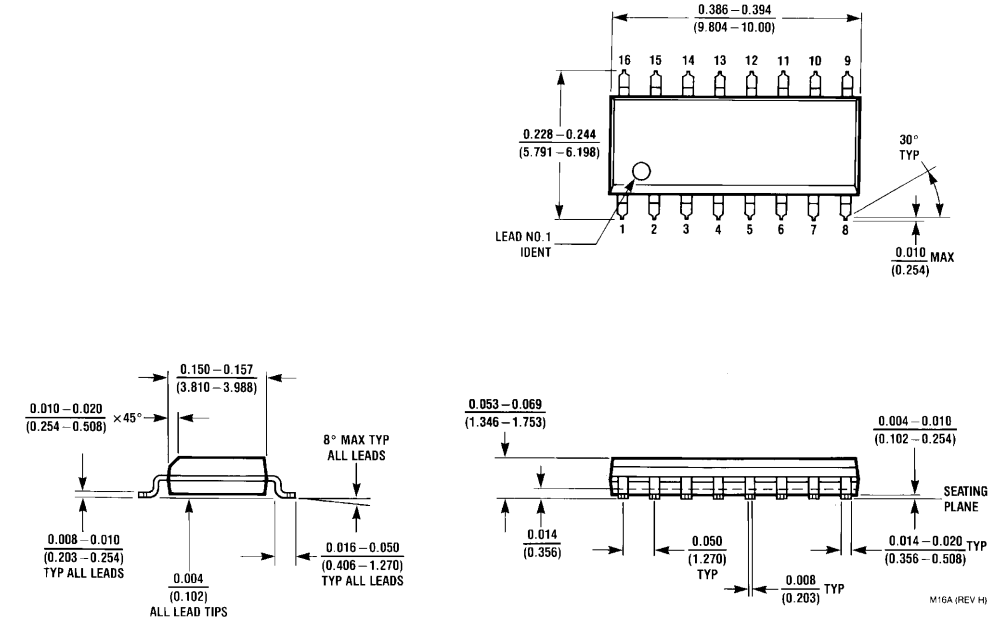
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_r = t_f = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

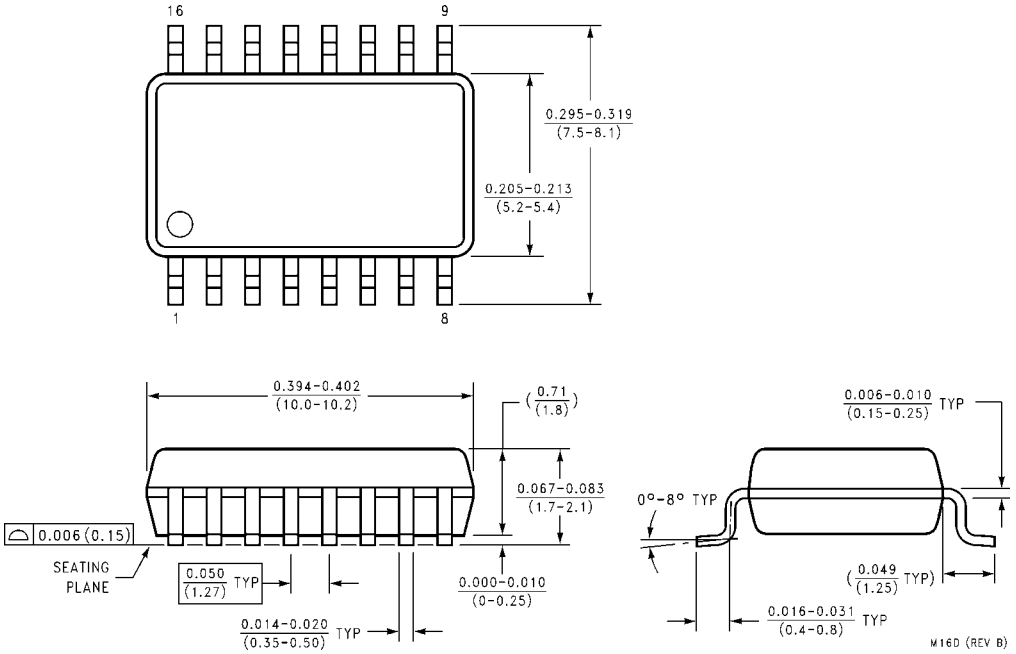
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

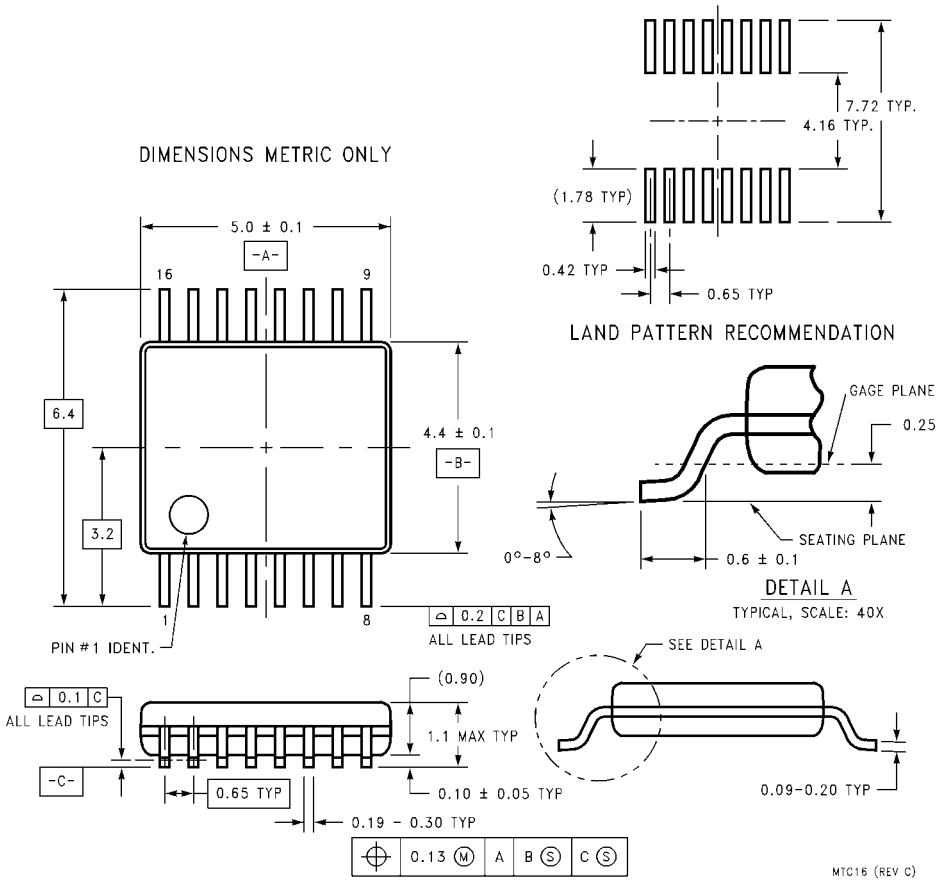


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX16240
Low Voltage 16-Bit Inverting Buffer/Line Driver with 5V Tolerant Inputs/Outputs

General Description

The LCX16240 contains sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The LCX16240 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capacity of interfacing to a 5V signal environment.

The LCX16240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

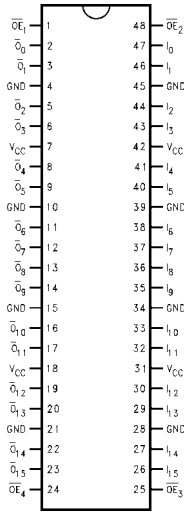
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

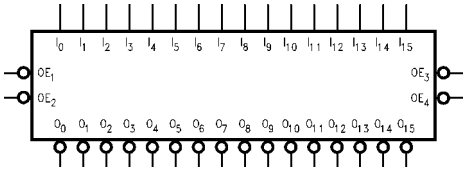
Order Number	Package Number	Package Description
74LCX16240MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

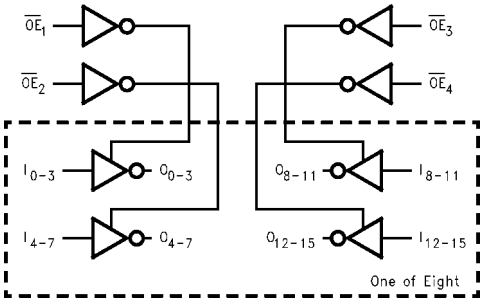
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The LCX16240 contains sixteen inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5 \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	4.5	1.5	5.3	1.5	5.4	ns
t_{PLH}	Data to Output	1.5	4.5	1.5	5.3	1.5	5.4	
t_{PZL}	Output Enable Time	1.5	5.4	1.5	6.0	1.5	7.0	ns
t_{PZH}		1.5	5.4	1.5	6.0	1.5	7.0	
t_{PLZ}	Output Disable Time	1.5	5.3	1.5	5.4	1.5	6.4	ns
t_{PHZ}		1.5	5.3	1.5	5.4	1.5	6.4	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Unit
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

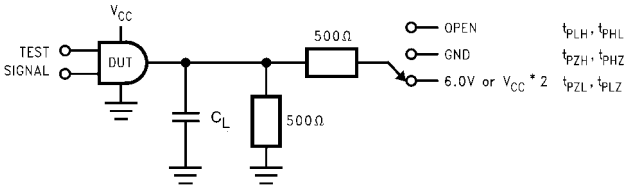
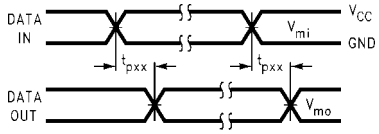
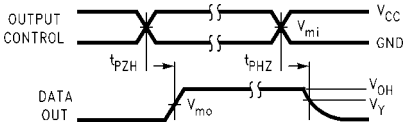


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

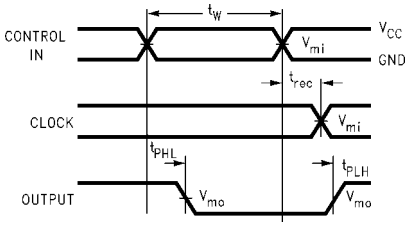
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



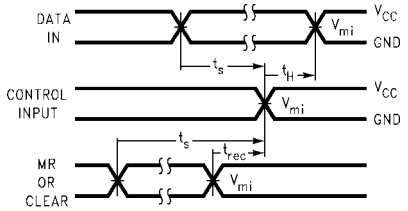
Waveform for Inverting and Non-Inverting Functions



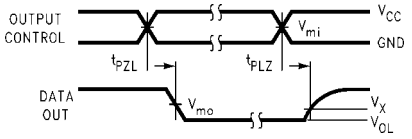
3-STATE Output High Enable and Disable Times for Logic



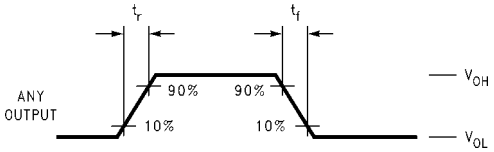
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

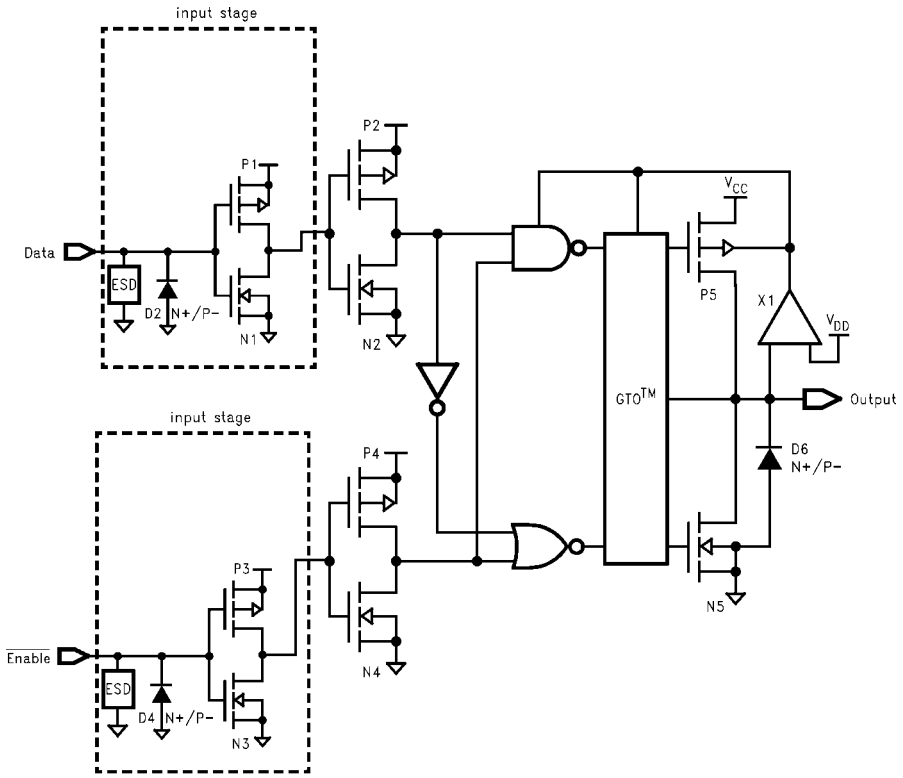


t_{rise} and t_{fall}

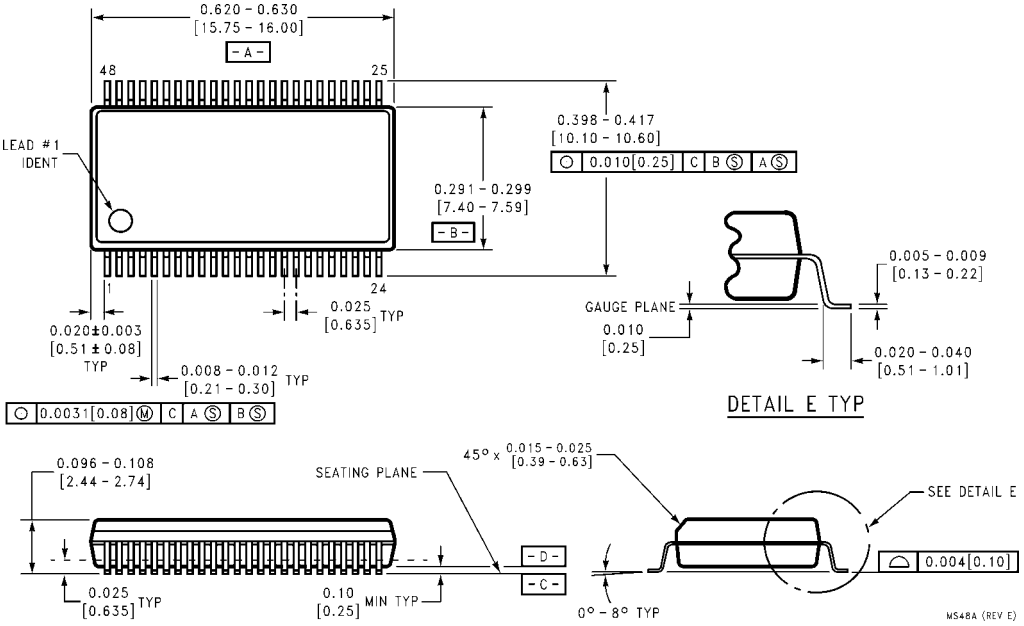
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

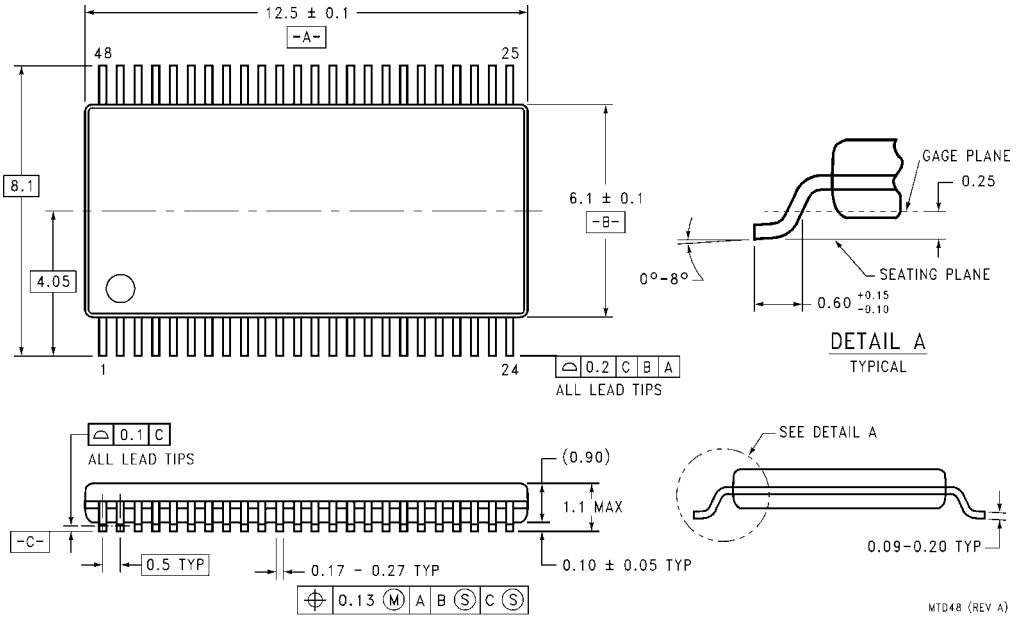


Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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February 1994
Revised April 1999

74LCX16244

Low Voltage 16-Bit Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX16244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The LCX16244 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max (V_{CC} = 3.0V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

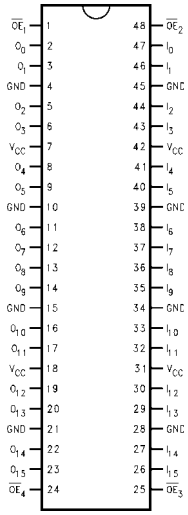
Note 1: To ensure the high-impedance state during power up or down $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

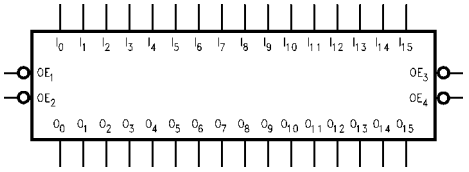
Order Number	Package Number	Package Description
74LCX16244MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

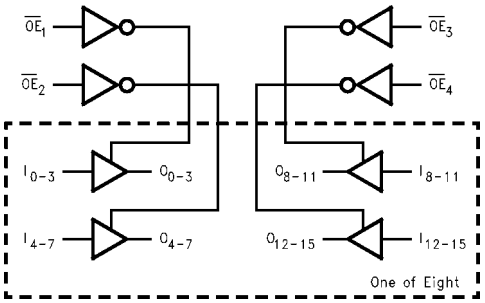
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The LCX16244 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	4.5	1.5	5.2	1.5	5.4	ns
t_{PLH}	Data to Output	1.5	4.5	1.5	5.2	1.5	5.4	
t_{PZL}	Output Enable Time	1.5	5.5	1.5	6.3	1.5	7.2	ns
t_{PZH}		1.5	5.5	1.5	6.3	1.5	7.2	
t_{PLZ}	Output Disable Time	1.5	5.4	1.5	5.7	1.5	6.5	ns
t_{PHZ}		1.5	5.4	1.5	5.7	1.5	6.5	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

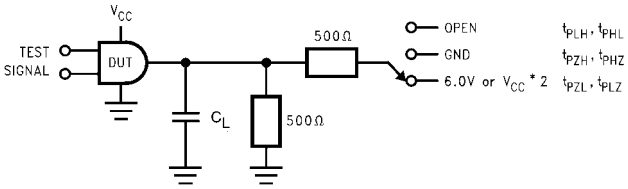
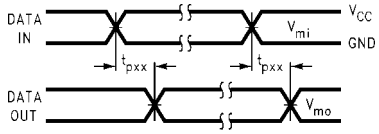
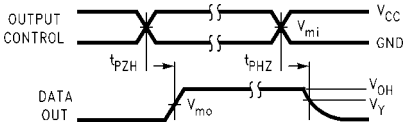


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

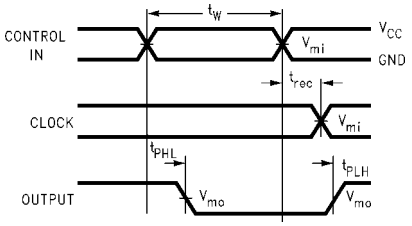
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



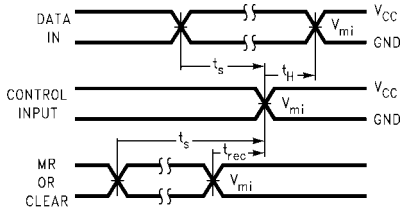
Waveform for Inverting and Non-Inverting Functions



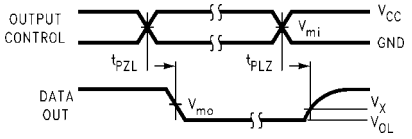
3-STATE Output High Enable and Disable Times for Logic



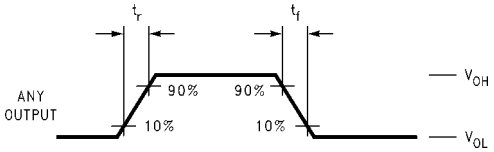
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

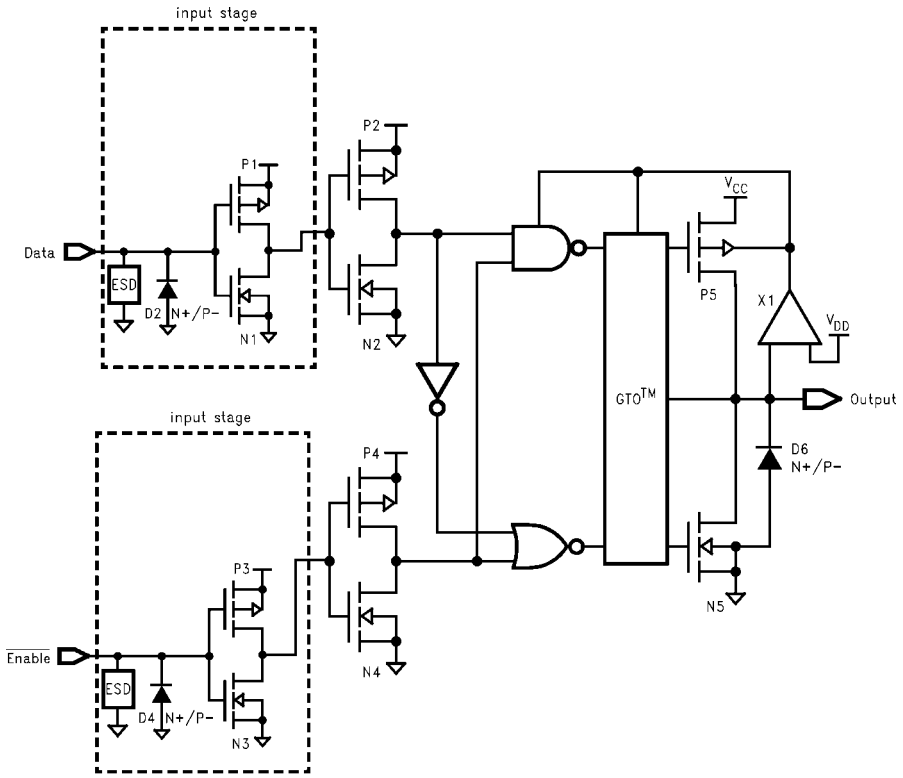


t_{rise} and t_{fall}

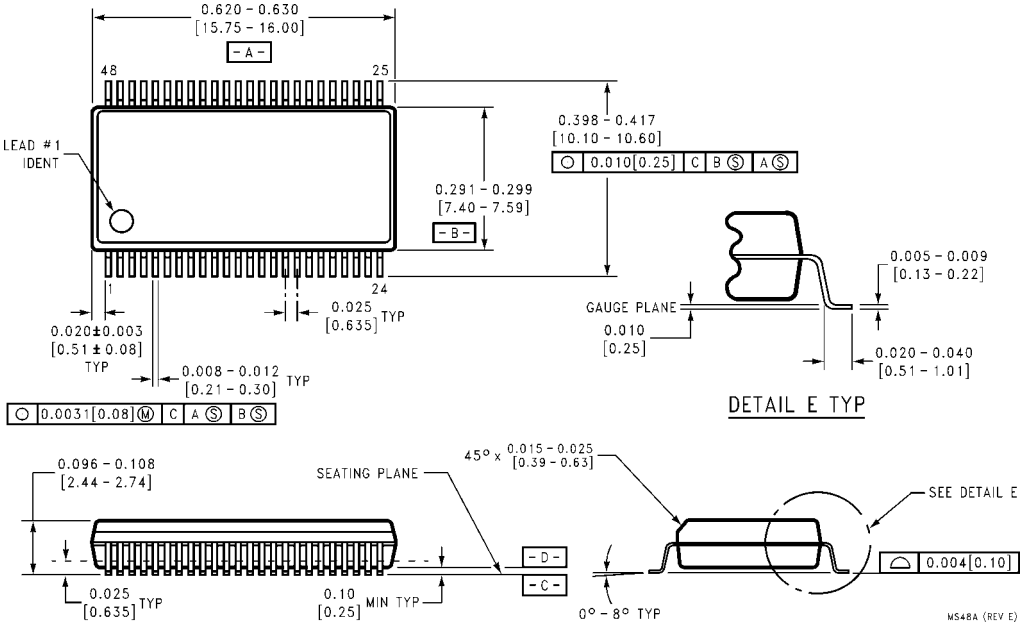
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

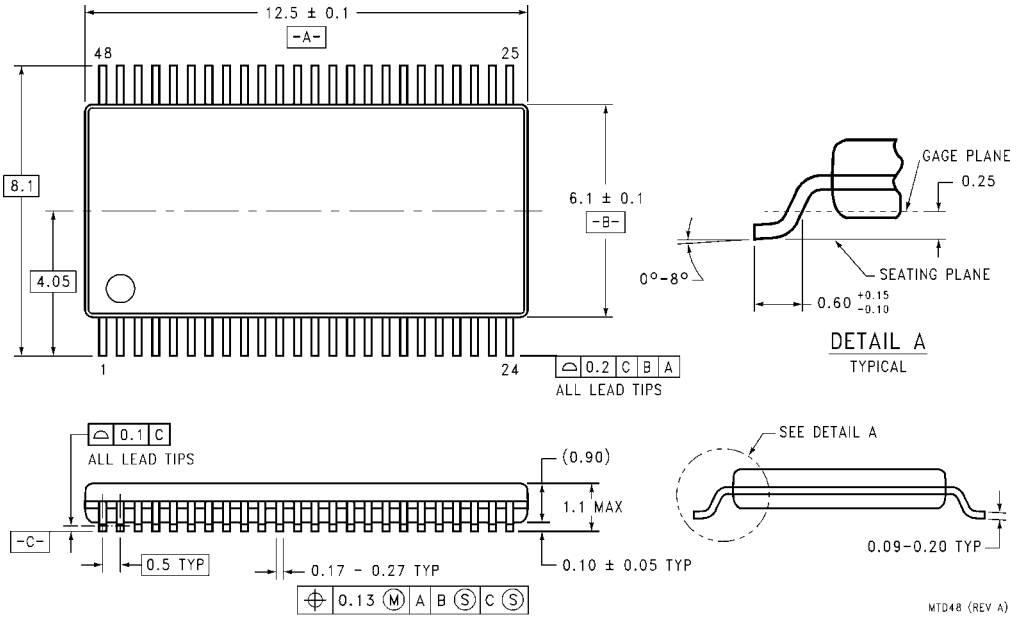


Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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February 1994
Revised April 1999

74LCX16245
Low Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The $T/\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The LCX16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

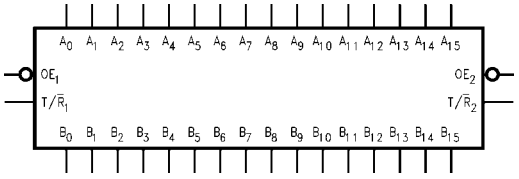
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

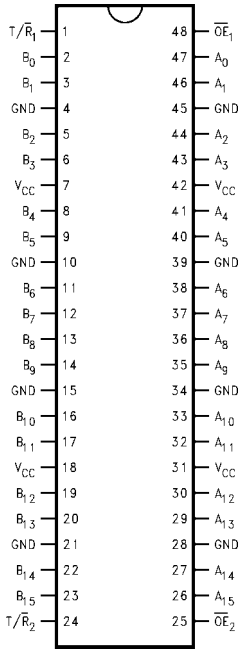
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

Connection Diagram



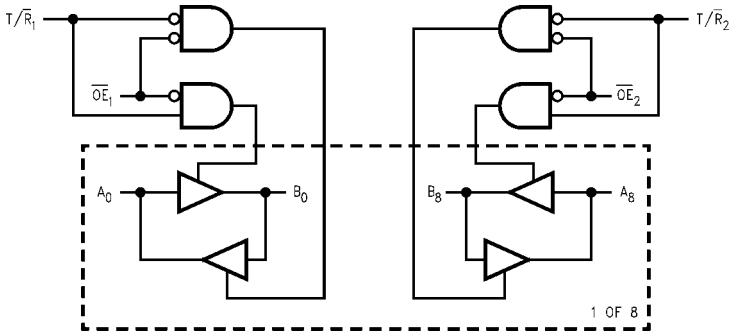
Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH Z State on A_8–A_{15}, B_8–B_{15}

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/O's must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–3.6		20	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3–3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	4.5	1.5	5.2	1.5	5.4	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	4.5	1.5	5.2	1.5	5.4	
t_{PZL}	Output Enable Time	1.5	6.5	1.5	7.2	1.5	8.5	ns
t_{PZH}		1.5	6.5	1.5	7.2	1.5	8.5	
t_{PLZ}	Output Disable Time	1.5	6.4	1.5	6.9	1.5	7.7	ns
t_{PHZ}		1.5	6.4	1.5	6.9	1.5	7.7	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

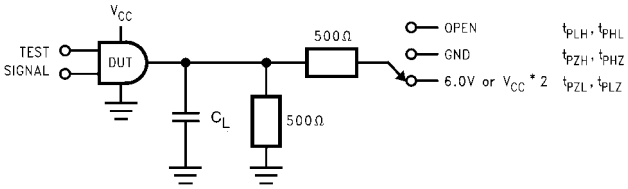
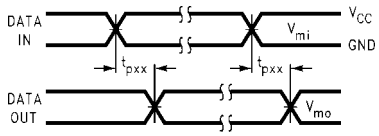
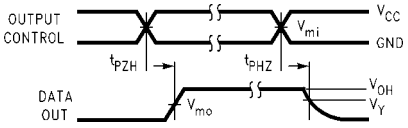


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

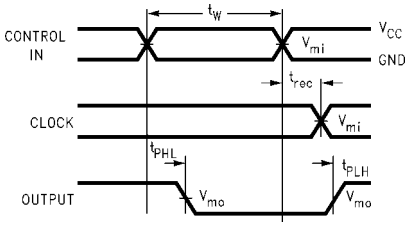
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



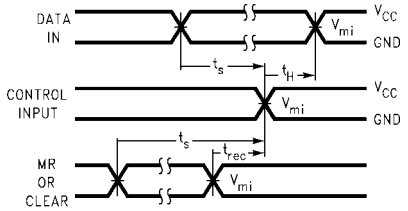
Waveform for Inverting and Non-Inverting Functions



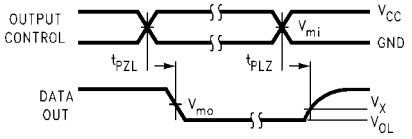
3-STATE Output High Enable and Disable Times for Logic



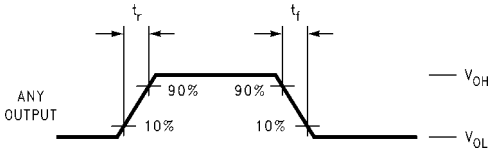
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

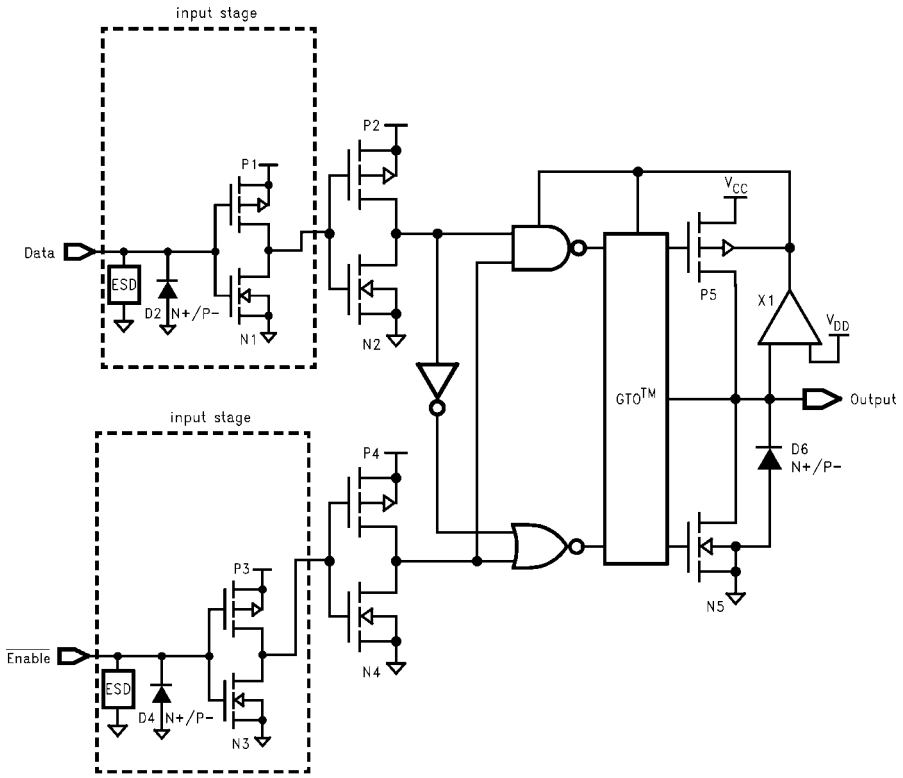


t_{rise} and t_{fall}

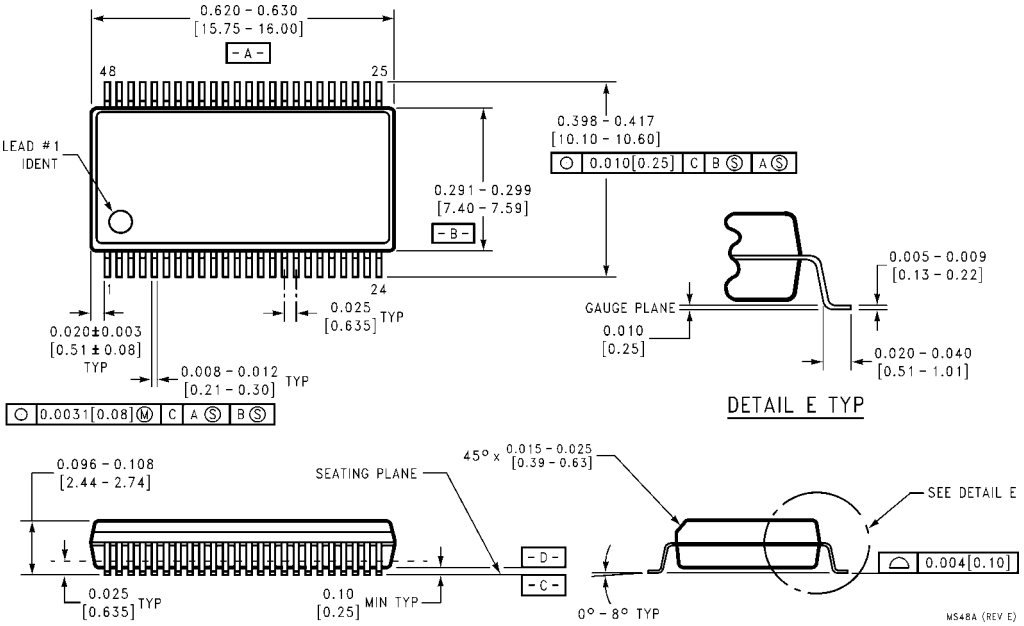
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

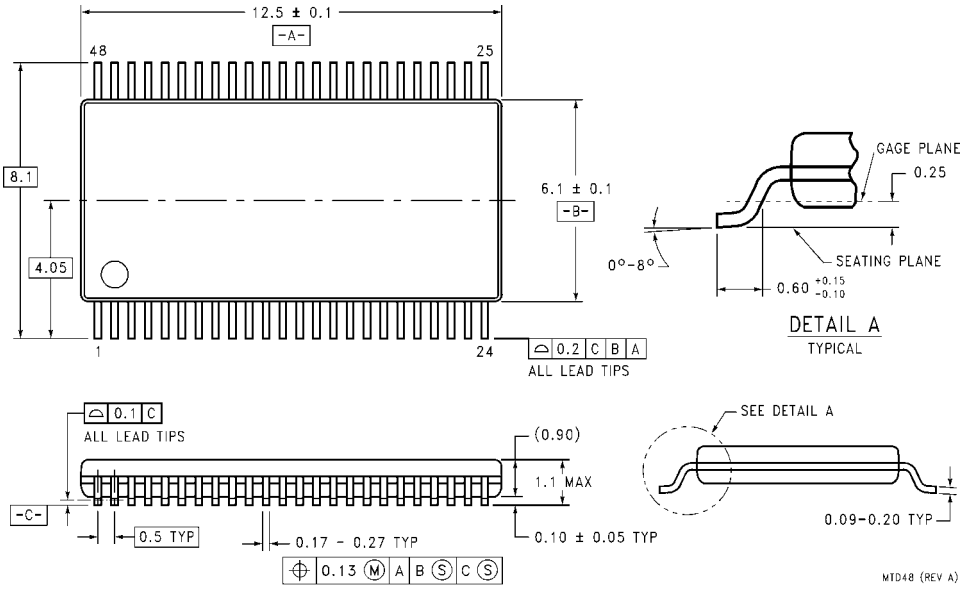


Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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February 1994
Revised April 1999

74LCX16373

Low Voltage 16-Bit Transparent Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The LCX16373 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.4 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

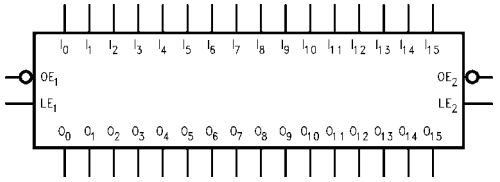
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

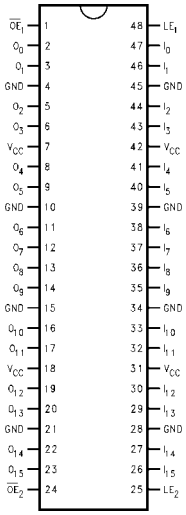
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

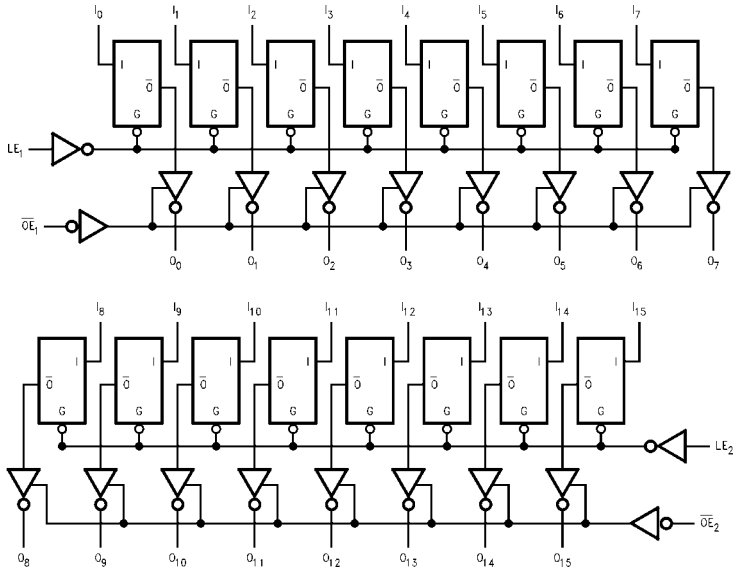
Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Functional Description

The LCX16373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagrams



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = 8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.4	1.5	5.9	1.5	6.5	ns
t_{PLH}	I_n to O_n	1.5	5.4	1.5	5.9	1.5	6.5	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.4	1.5	6.6	ns
t_{PLH}	LE to O_n	1.5	5.5	1.5	6.4	1.5	6.6	
t_{PZL}	Output Enable Time	1.5	6.1	1.5	6.5	1.5	7.9	ns
t_{PZH}		1.5	6.1	1.5	6.5	1.5	7.9	
t_{PLZ}	Output Disable Time	1.5	6.0	1.5	6.3	1.5	7.2	ns
t_{PHZ}		1.5	6.0	1.5	6.3	1.5	7.2	
t_S	Setup Time, I_n to LE	2.5		2.5		3.0		ns
t_H	Hold Time, I_n to LE	1.5		1.5		2.0		ns
t_W	LE Pulse Width	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

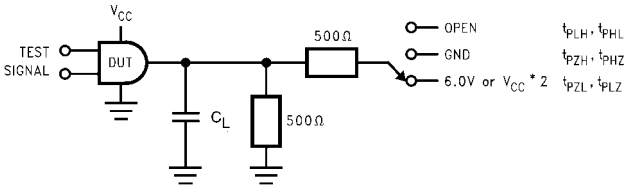
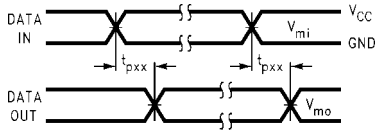
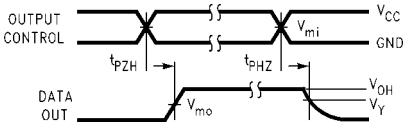


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

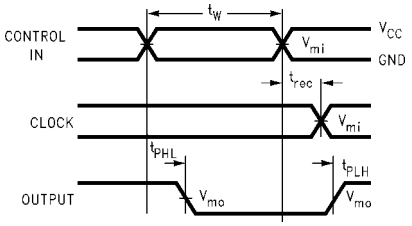
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



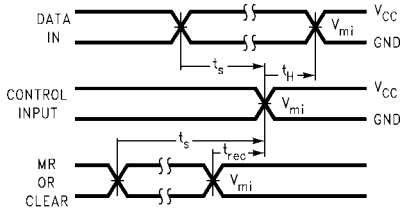
Waveform for Inverting and Non-Inverting Functions



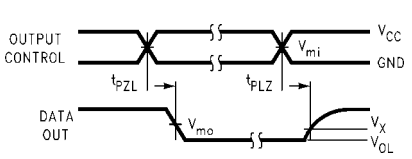
3-STATE Output High Enable and Disable Times for Logic



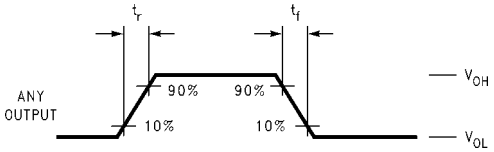
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

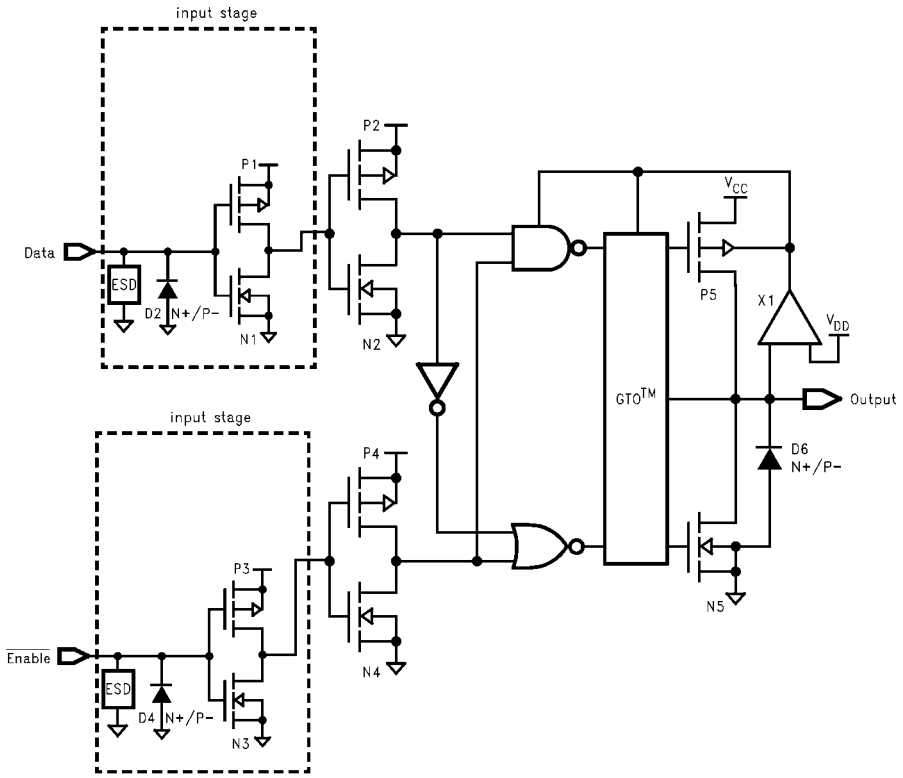


t_{rise} and t_{fall}

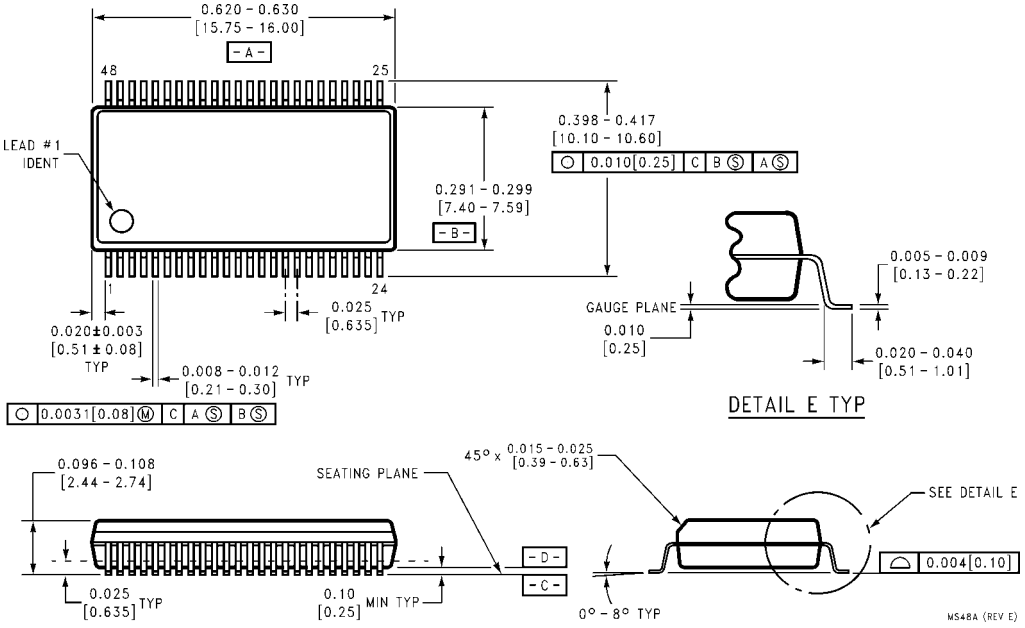
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

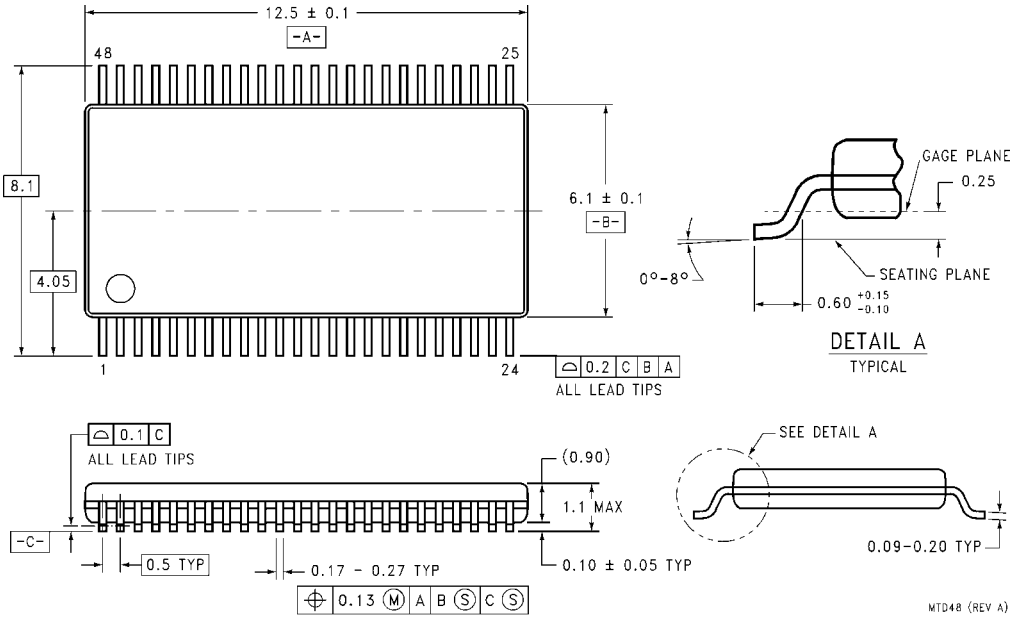


Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX16374

Low Voltage 16-Bit D-Type Flip-Flop with 5V Tolerant Inputs and Outputs

General Description

The LCX16374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and Output Enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

The LCX16374 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.2 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

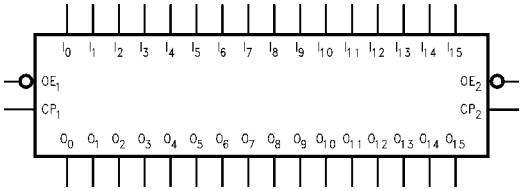
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

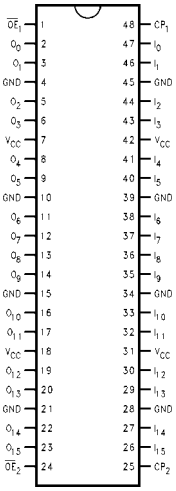
Order Number	Package Number	Package Description
74LCX16374MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Functional Description

The LCX16374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each byte has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}_n$ input does not affect the state of the flip-flops.

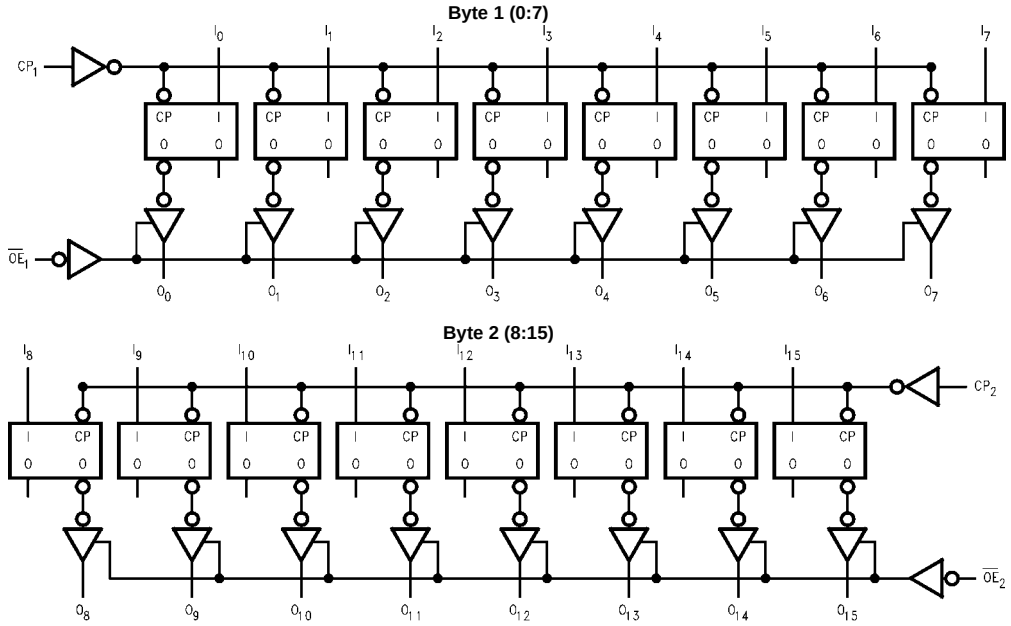
Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
↑	L	H	H
↑	L	L	L
L	L	X	O_0
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
↑	L	H	H
↑	L	L	L
L	L	X	O_0
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of CP

Logic Diagrams



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	μA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	μA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	170						MHz
t_{PHL}	Propagation Delay	1.5	6.2	1.5	6.5	1.5	7.4	ns
t_{PLH}	CP to O_n	1.5	6.2	1.5	6.5	1.5	7.4	
t_{PZL}	Output Enable time	1.5	6.1	1.5	6.3	1.5	7.9	ns
t_{PZH}		1.5	6.1	1.5	6.3	1.5	7.9	
t_{PLZ}	Output Disable Time	1.5	6.0	1.5	6.2	1.5	7.2	ns
t_{PHZ}		1.5	6.0	1.5	6.2	1.5	7.2	
t_S	Setup Time	2.5		2.5		3.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the differences between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

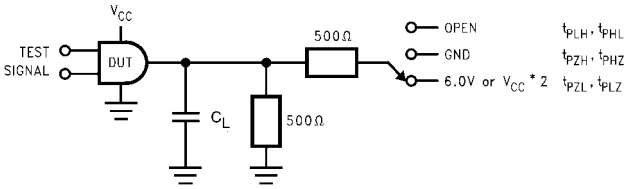
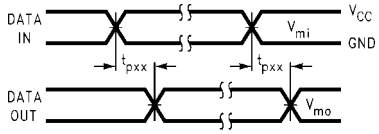
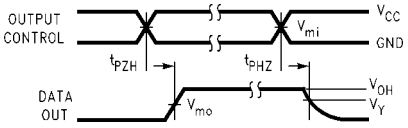


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

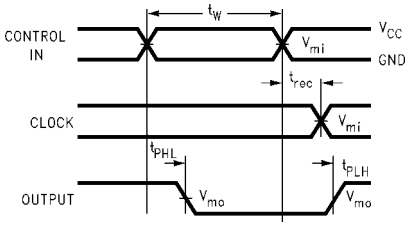
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



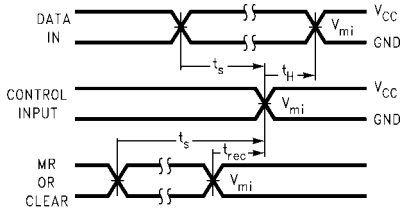
Waveform for Inverting and Non-Inverting Functions



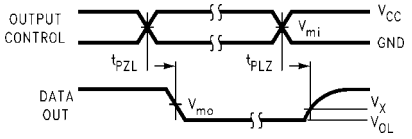
3-STATE Output High Enable and Disable Times for Logic



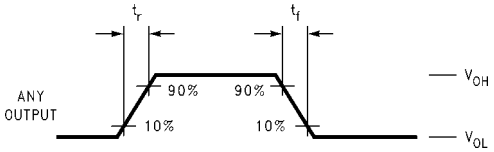
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

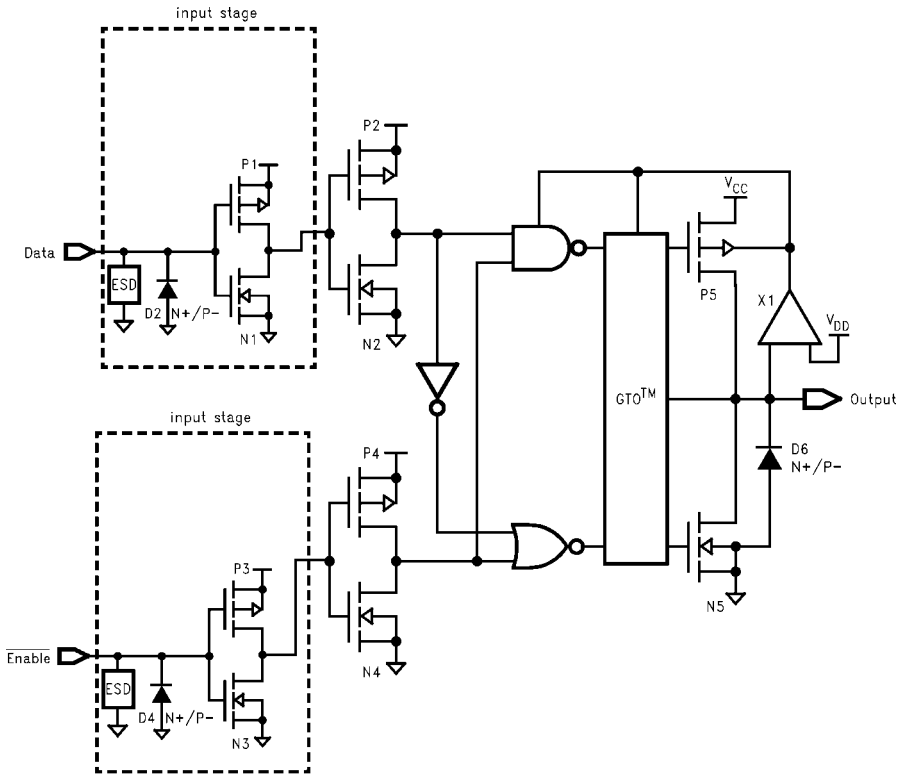


t_{rise} and t_{fall}

FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family



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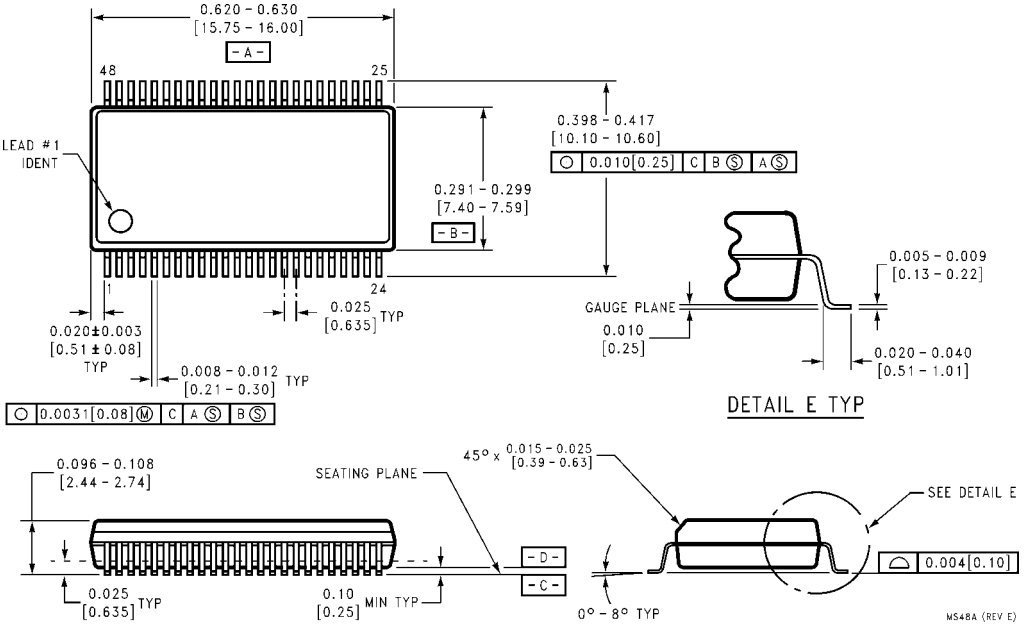
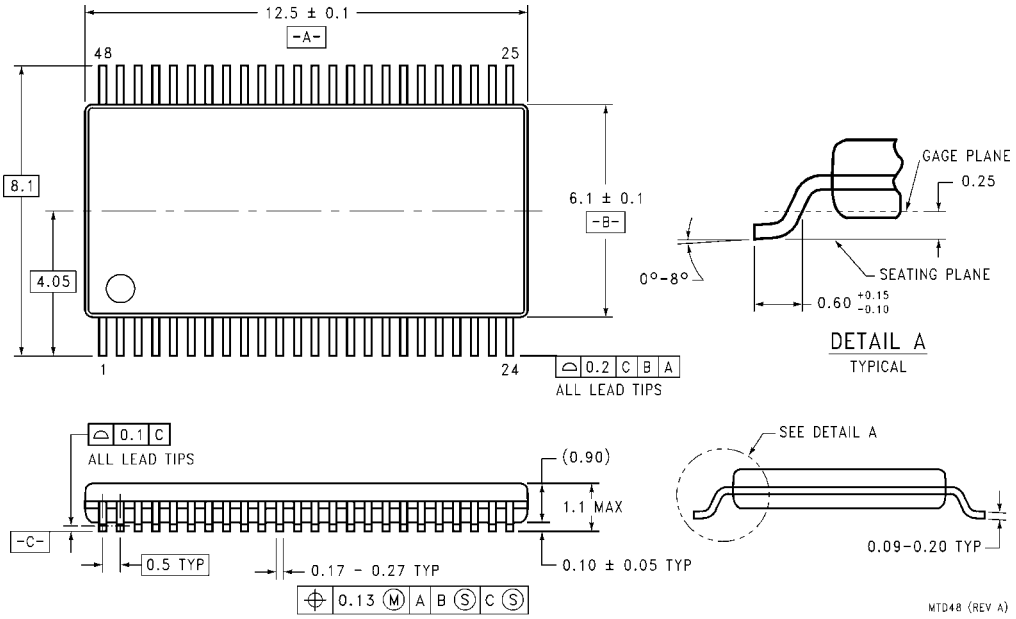


48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX16500
Low Voltage 18-Bit Universal Bus Transceivers with 5V Tolerant Inputs and Outputs

General Description

These 18-bit universal bus transceivers combine D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable ($\overline{OEAB}$ and $\overline{OEBA}$), latch-enable (LEAB and LEBA), and clock ($\overline{CLKAB}$ and $\overline{CLKBA}$) inputs.

The LCX16500 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with the capability of interfacing to a 5V signal environment.

The LCX16500 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0 ns t_{PD} max (V_{CC} = 3.3V), 20 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

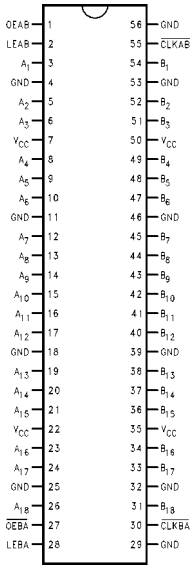
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} and OE tied to GND through a resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16500MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16500MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Truth Table (Note 2)

Inputs				Output
OEAB	**LEAB**	**$\overline{\text{CLKAB}}$**	**A_n**	**B_n**
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↓	L	L
H	L	↓	H	H
H	L	H	X	B_0 (Note 3)
H	L	L	X	B_0 (Note 4)

Note 2: A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{\text{OEBA}}$, LEBA, and $\overline{\text{CLKBA}}$.

Note 3: Output level before the indicated steady-state input conditions were established.

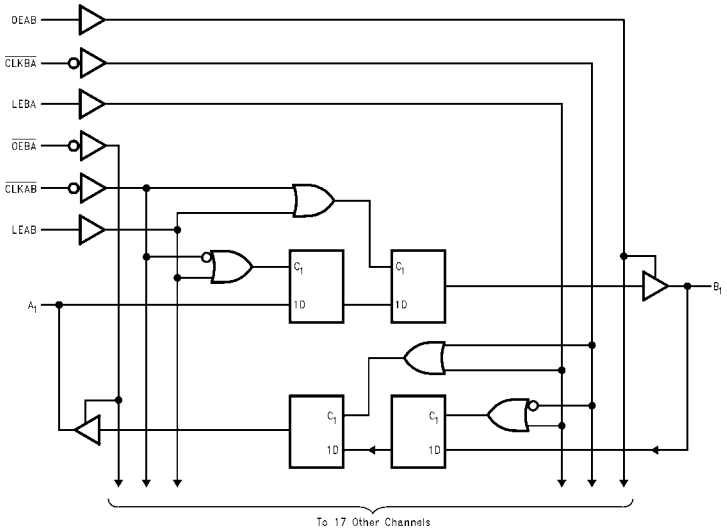
Note 4: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CLKAB}}$ was LOW before LEAB went LOW.

Functional Description

For A-to-B data flow, the LCX16500 operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if $\overline{\text{CLKAB}}$ is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the HIGH-to-LOW transition of $\overline{\text{CLKAB}}$. Output-enable OEAB is active-HIGH. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in the high impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{\text{OEBA}}$, LEBA, and $\overline{\text{CLKBA}}$. The output enables are complementary (OEAB is active HIGH and $\overline{\text{OEBA}}$ is active LOW).

Logic Diagram



Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 6)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 7)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 5: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 8)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 8: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	170						MHz
t_{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PLH}	Bus to Bus	1.5	6.0	1.5	7.0	1.5	7.2	
t_{PHL}	Propagation Delay	1.5	6.7	1.5	8.0	1.5	8.4	ns
t_{PLH}	Clock to Bus	1.5	6.7	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	LE to Bus	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PZL}	Output Enable Time	1.5	7.2	1.5	8.2	1.5	9.4	ns
t_{PZH}		1.5	7.2	1.5	8.2	1.5	9.4	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	8.0	1.5	8.4	
t_S	Setup Time	2.5		2.5		3.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 9)		1.0					

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}), or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

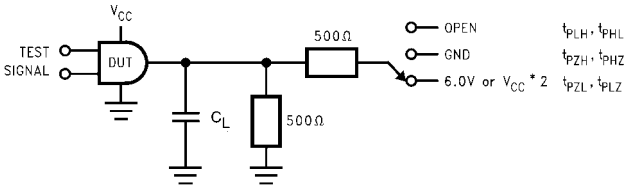
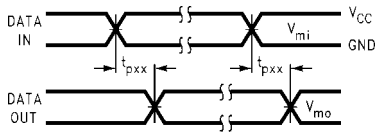
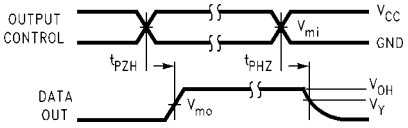


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

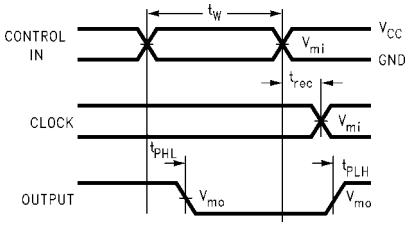
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



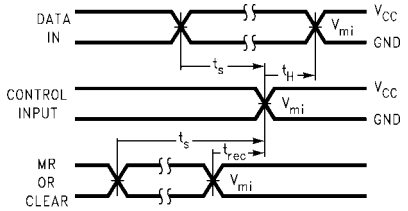
Waveform for Inverting and Non-Inverting Functions



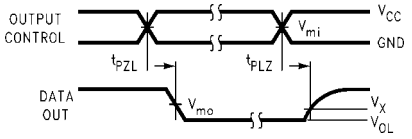
3-STATE Output High Enable and Disable Times for Logic



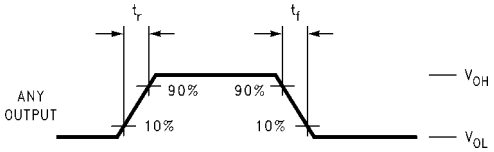
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

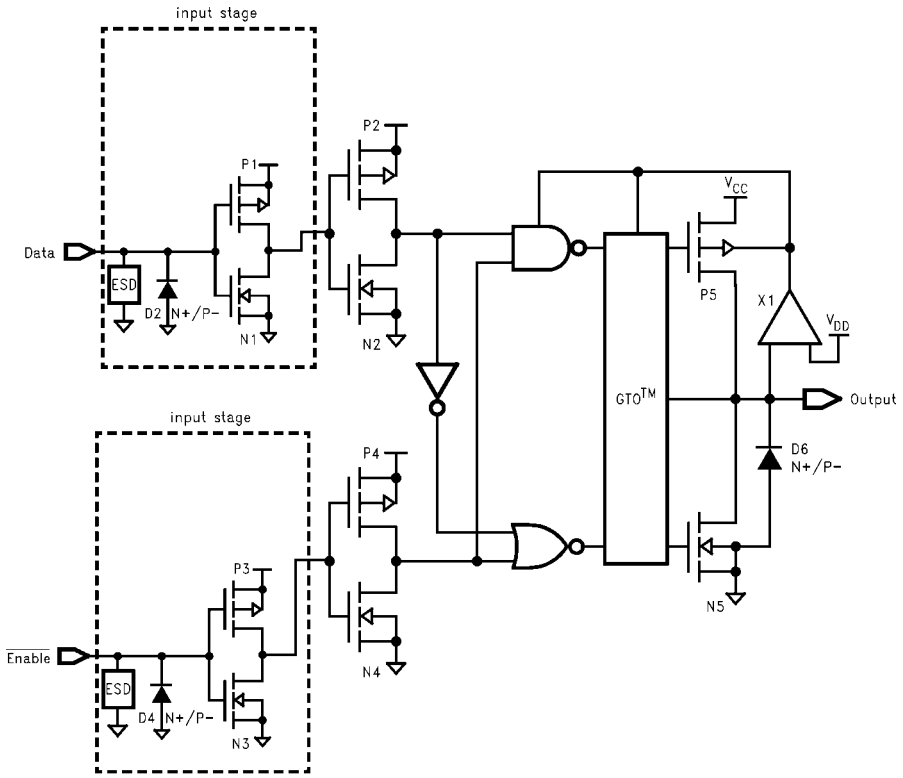


t_{rise} and t_{fall}

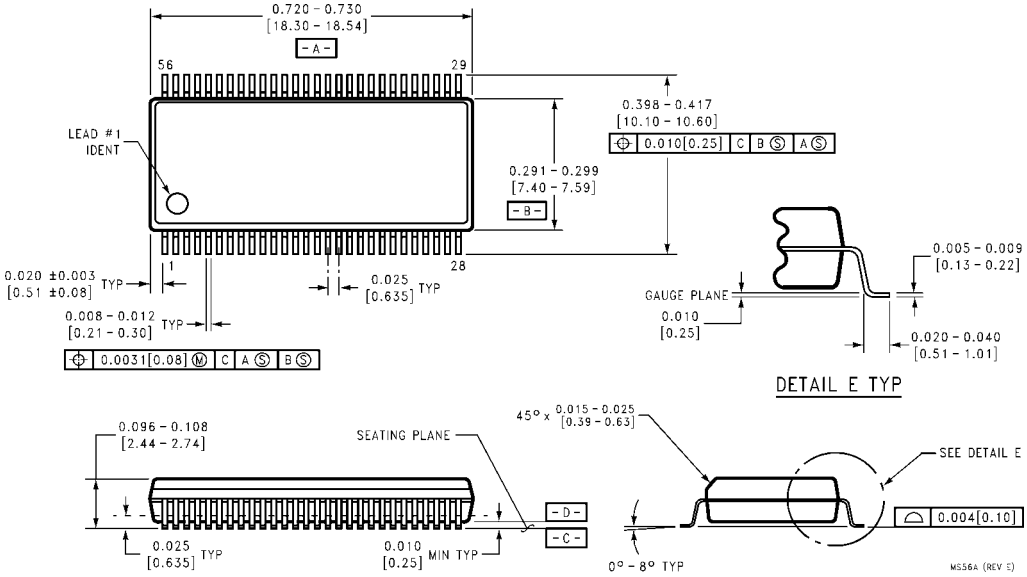
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

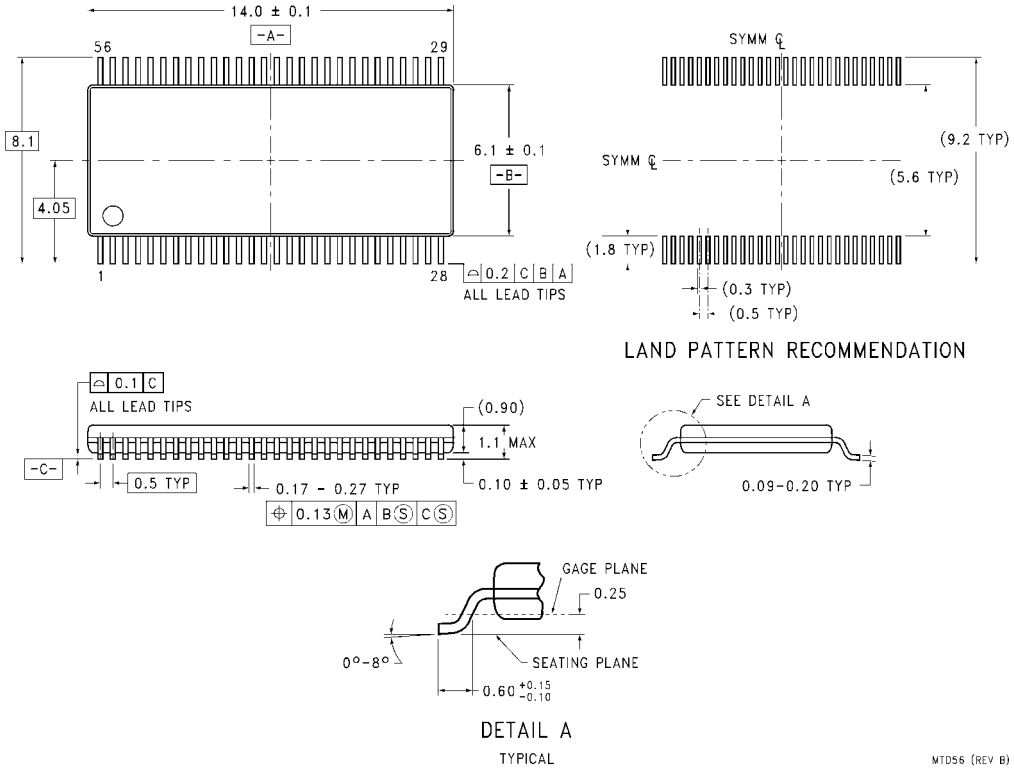


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1995
Revised April 1999

74LCX16501

18-Bit Universal Bus Transceivers with 5V Tolerant Inputs and Outputs

General Description

The LCX16501 is an 18-bit universal bus transceiver combining D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and $\overline{\text{OEBA}}$), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs.

The LCX16501 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16501 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA Output Drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model < 200V

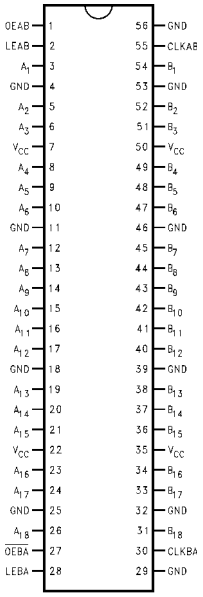
Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} and OE tied to GND through a resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16501MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16501MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Truth Table (Note 2)

Inputs				Output
OEAB	**LEAB**	**CLKAB**	**A_n**	**B_n**
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↑	L	L
H	L	↑	H	H
H	L	H	X	B_0 (Note 3)
H	L	L	X	B_0 (Note 4)

Note 2: A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{\text{OEBA}}$, LEBA, and CLKBA.

Note 3: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

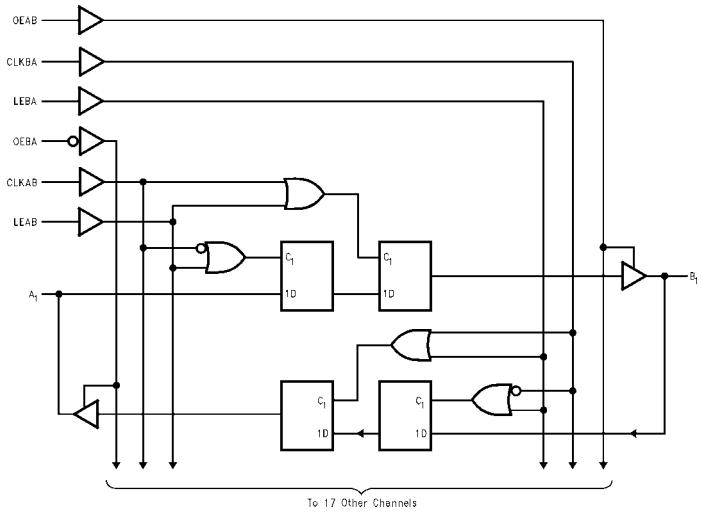
Note 4: Output level before the indicated steady-state input conditions were established.

Functional Description

For A-to-B data flow, the LCX16501 operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a high or low logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in the high impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{\text{OEBA}}$, LEBA, and CLKBA. The output enables are complementary (OEAB is active HIGH and $\overline{\text{OEBA}}$ is active LOW).

Logic Diagram



Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 6)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 7)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 5: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Unused (inputs or I/Os) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 8)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3– 3.6		500	µA

Note 8: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	170						MHz
t_{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PLH}	Bus to Bus	1.5	6.0	1.5	7.0	1.5	7.2	
t_{PHL}	Propagation Delay	1.5	6.7	1.5	8.0	1.5	8.4	ns
t_{PLH}	Clock to Bus	1.5	6.7	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	LE to Bus	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PZL}	Output Enable Time	1.5	7.2	1.5	8.2	1.5	9.4	ns
t_{PZH}		1.5	7.2	1.5	8.2	1.5	9.4	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	8.0	1.5	8.4	
t_S	Setup Time	2.5		2.5		3.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 9)		1.0					

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}), or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

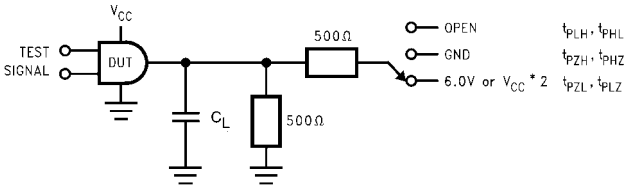
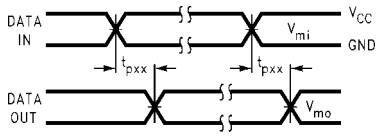
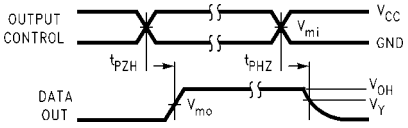


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

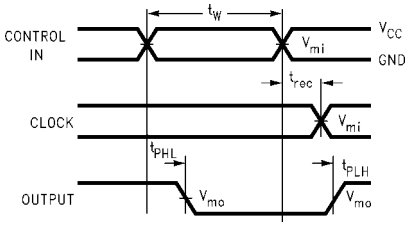
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



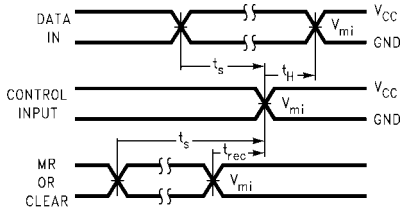
Waveform for Inverting and Non-Inverting Functions



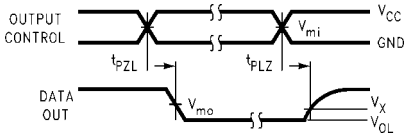
3-STATE Output High Enable and Disable Times for Logic



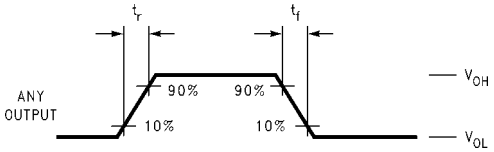
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

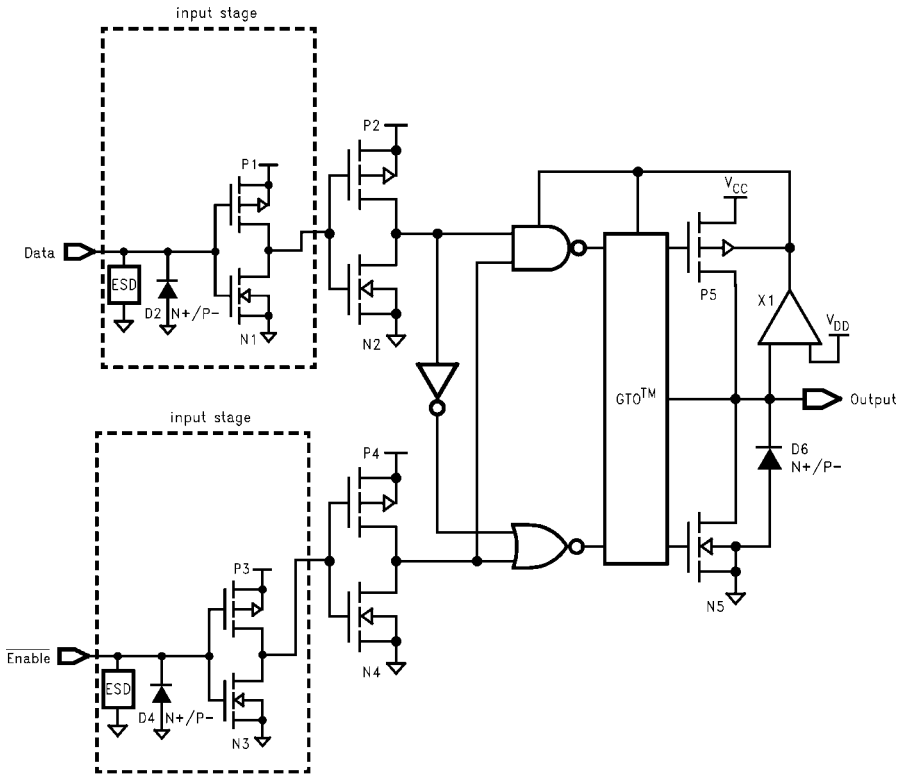


t_{rise} and t_{fall}

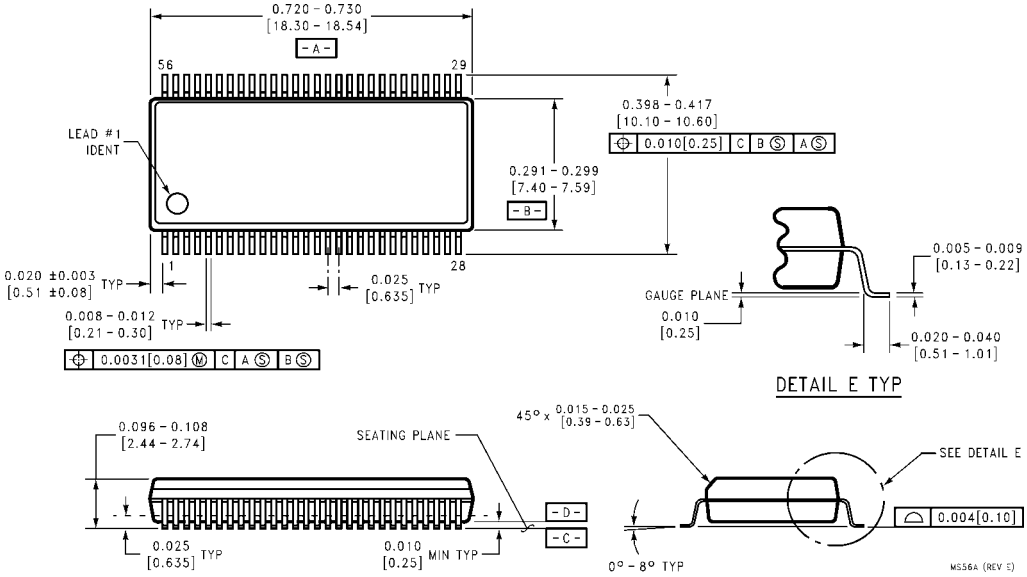
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

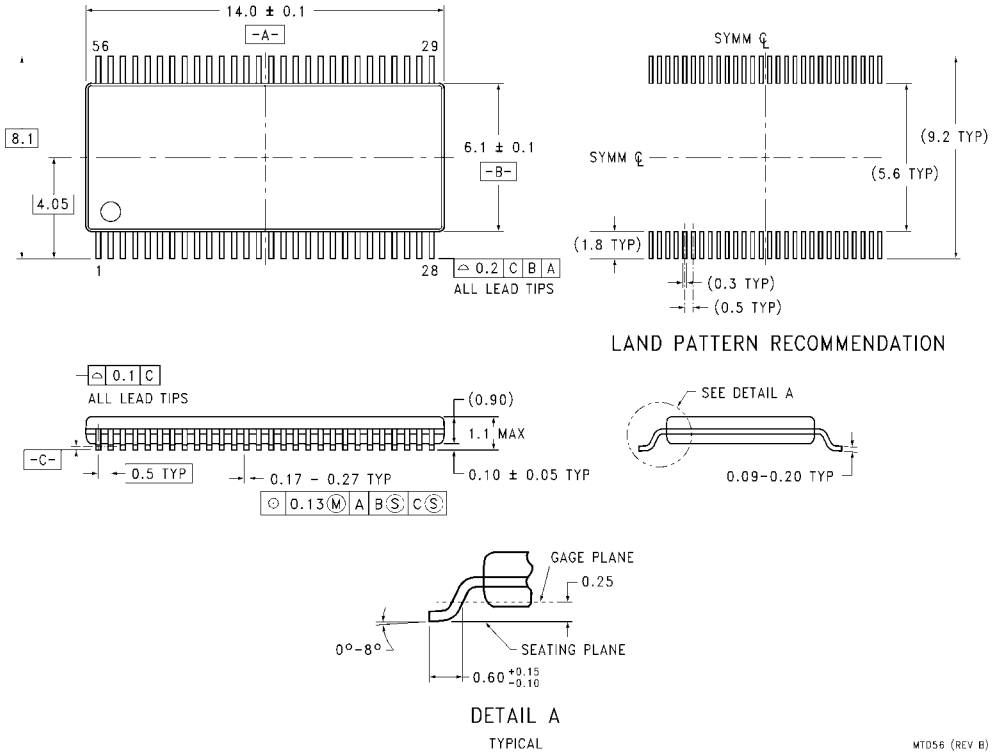


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

May 1995
Revised April 1999

74LCX16543
Low Voltage 16-Bit Registered Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX16543 contains sixteen non-inverting transceivers containing two sets of D-type registers for temporary storage of data flowing in either direction. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The LCX16543 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16543 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.2 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA Output Drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human Body Model > 2000V
  - Machine Model > 200V

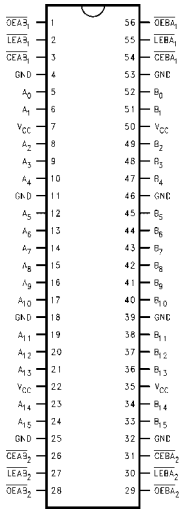
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

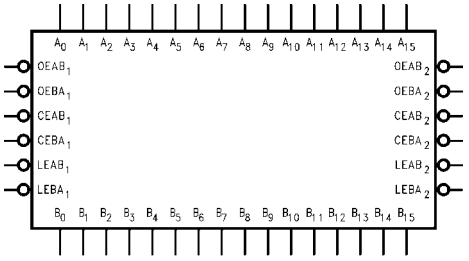
Order Number	Package Number	Package Description
74LCX16543MEA	MS56A	56-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16543MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OEAB}_n$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}_n$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}_n$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}_n$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}_n$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}_n$	B-to-A Latch Enable Input (Active LOW)
A_0–A_{15}	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B_0–B_{15}	B-to-A Data Inputs or A-to-B 3-STATE Outputs

Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}_n$	$\overline{LEAB}_n$	$\overline{OEAB}_n$	(Byte n)	(Byte n)
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

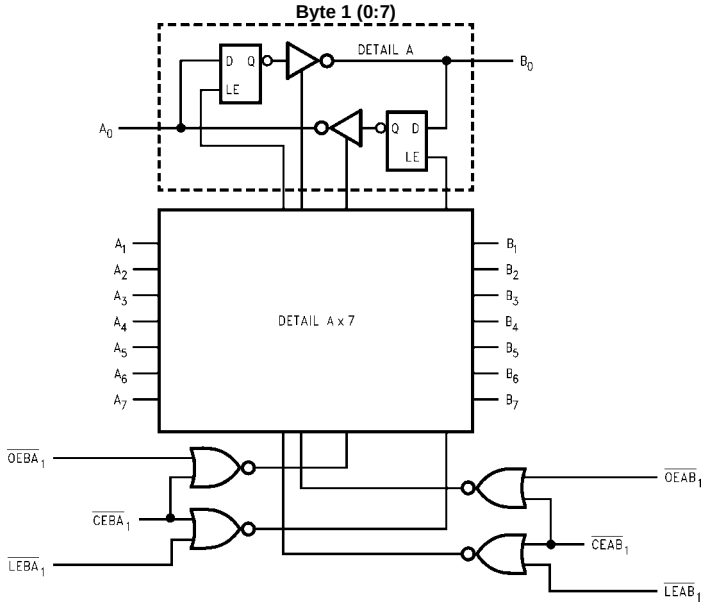
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$

Functional Description

The LCX16543 contains sixteen non-inverting transceivers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The following description applies to each byte. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}_n$) input must be LOW in order to enter data from A_0–A_{15} or take data from B_0–B_{15}, as indicated in the Data I/O Control Table. With $\overline{CEAB}_n$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}_n$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}_n$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}_n$ and $\overline{OEAB}_n$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$ inputs.

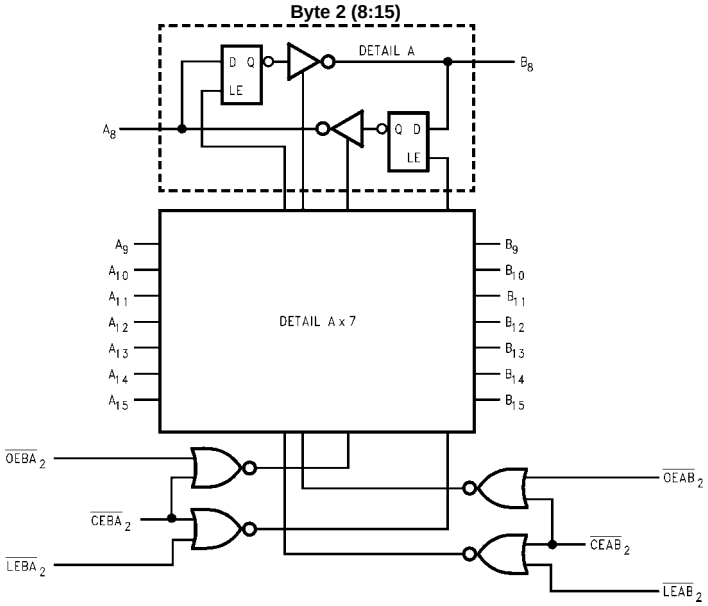
Logic Diagrams

Byte 1 (0:7)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to +7.0 –0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused (inputs or I/Os) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = –40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = –8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs in disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.2	1.5	6.0	1.5	6.2	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	5.2	1.5	6.0	1.5	6.2	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}	$\overline{LEBA}_n$ to A_n or $\overline{LEAB}_n$ to B_n	1.5	6.5	1.5	7.5	1.5	7.8	
t_{PZL}	Output Enable Time							ns
t_{PZH}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n	1.5	6.5	1.5	7.0	1.5	8.5	
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n	1.5	6.5	1.5	7.0	1.5	8.5	
t_{PLZ}	Output Disable Time							ns
t_{PHZ}	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to A_n or B_n	1.5	6.5	1.5	7.0	1.5	7.8	
	$\overline{CEBA}_n$ or $\overline{CEAB}_n$ to A_n or B_n	1.5	6.5	1.5	7.0	1.5	7.8	
t_S	Setup Time, HIGH or LOW, Data to $\overline{LEXX}_n$	2.5		2.5		3.0		ns
t_H	Hold Time, HIGH or LOW, Data to $\overline{LEXX}_n$	1.5		1.5		2.0		ns
t_W	Pulse Width, Latch Enable, LOW	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

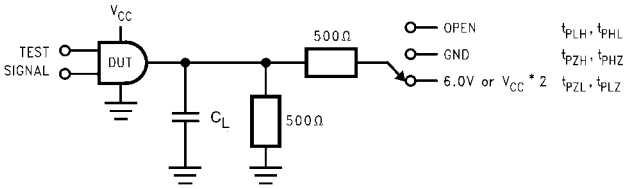
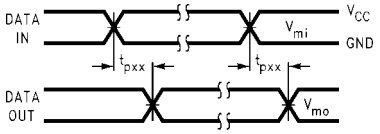
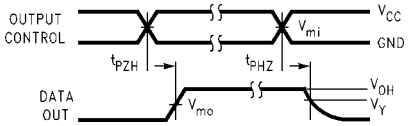


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

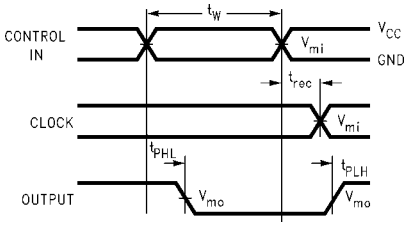
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



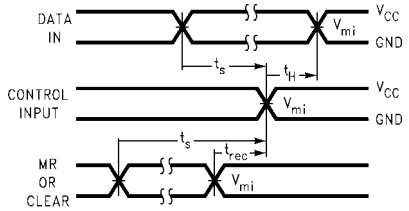
Waveform for Inverting and Non-Inverting Functions



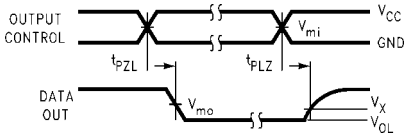
3-STATE Output High Enable and Disable Times for Logic



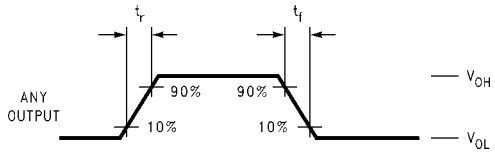
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

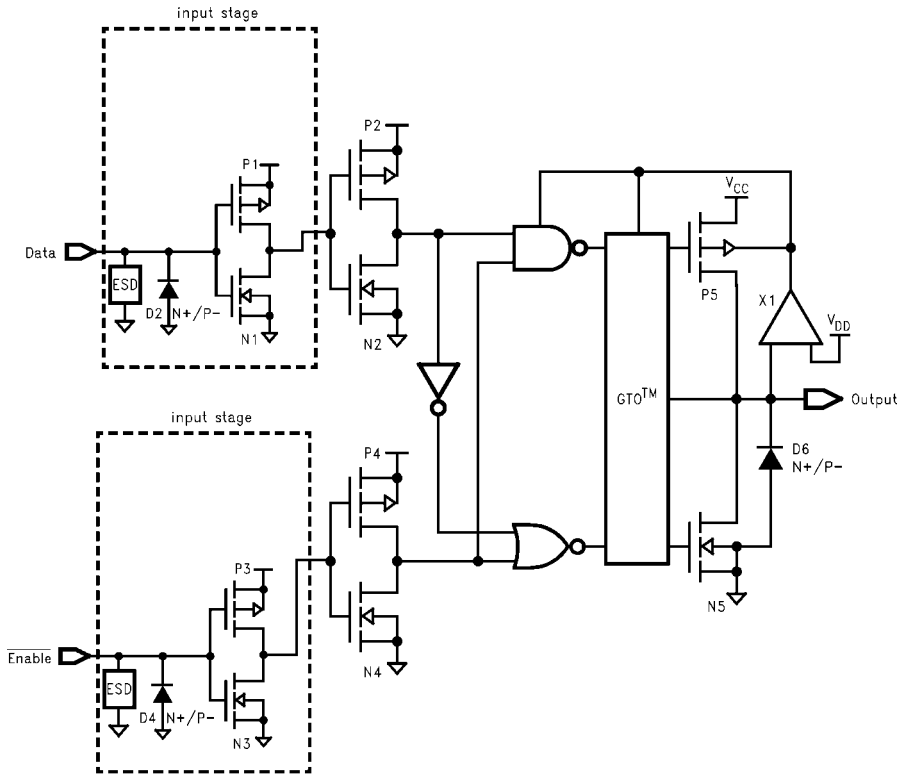


t_{rise} and t_{fall}

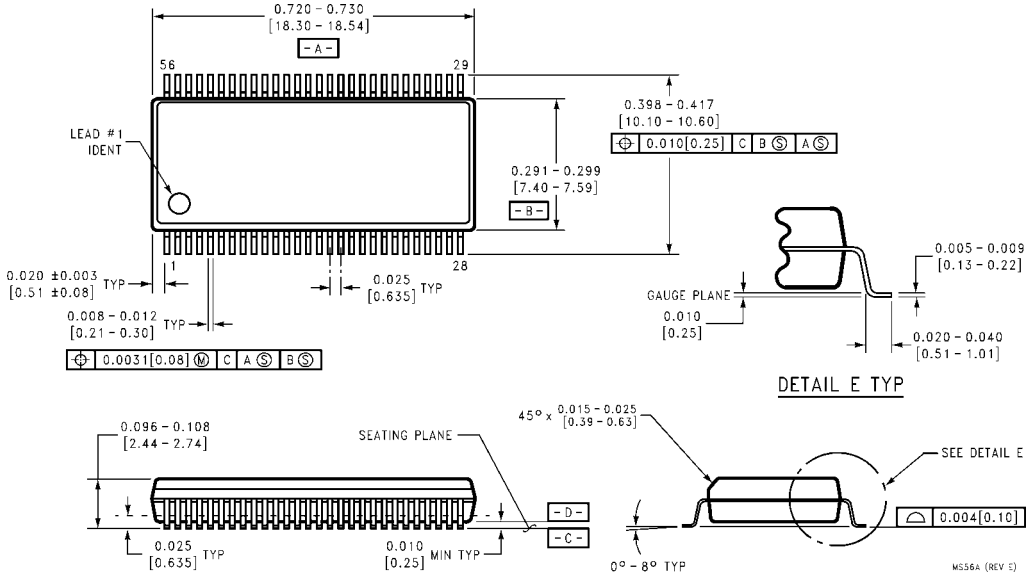
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

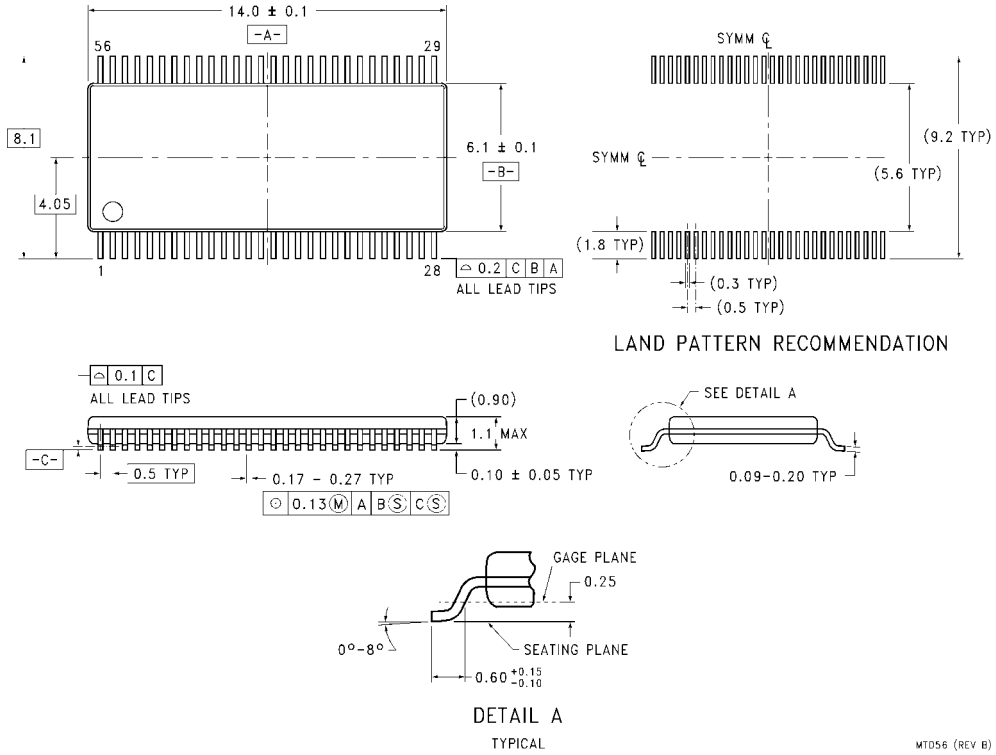


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX16646
Low Voltage 16-Bit Transceiver/Register with 5V Tolerant Inputs and Outputs

General Description

The LCX16646 contains sixteen non-inverting bidirectional registered bus transceivers with 3-STATE outputs, providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation.The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition (see Functional Description).

The LCX16646 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16646 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.2 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA Output Drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human Body Model > 2000V
  Machine Model > 200V

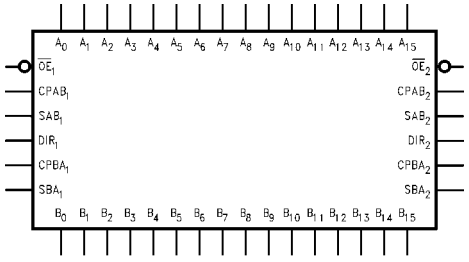
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16646MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16646MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

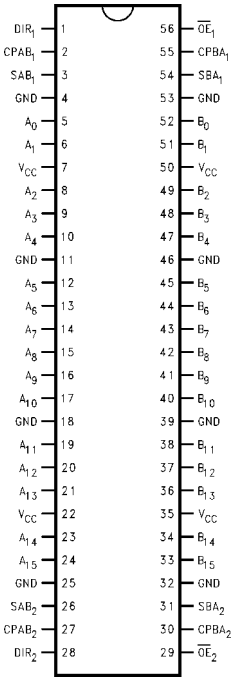
Logic Symbol



Pin Descriptions

Pin Names	Description
A_n	Side A Inputs or 3-STATE Outputs
B_n	Side B Inputs or 3-STATE Outputs
$\overline{OE}_n$	Output Enable Inputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
DIR_n	Direction Control Inputs

Connection Diagram



Truth Table

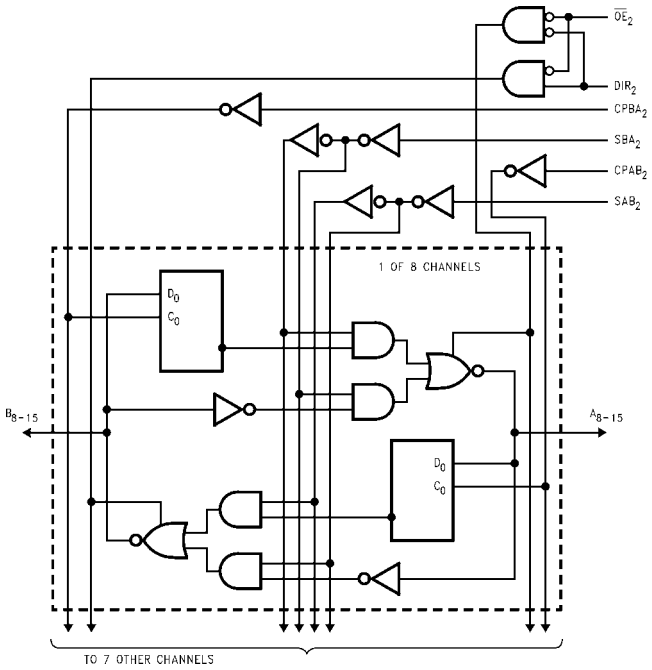
(Note 2)

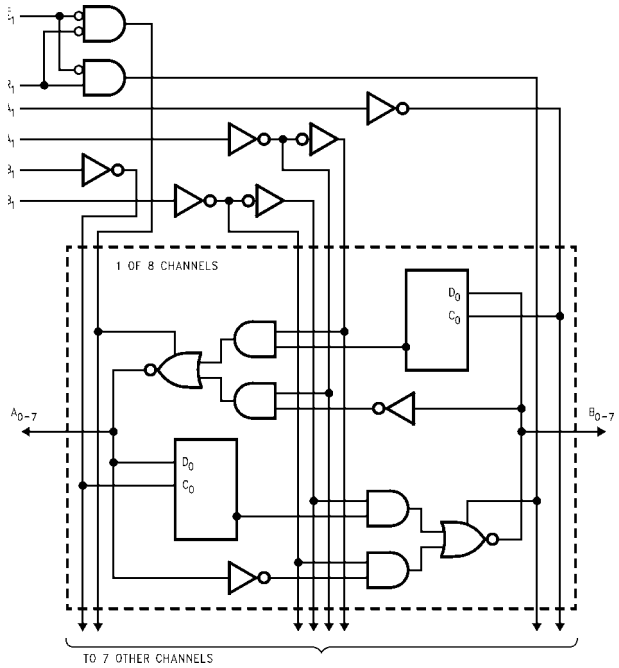
Inputs						Data I/O		Output Operation Mode
$\overline{OE}_1$	DIR_1	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_{0-7}	B_{0-7}	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data Into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data to A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n into B Register and Output to A_n

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level ↑ = LOW-to-HIGH Transition.

Note 2: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

Logic Diagrams





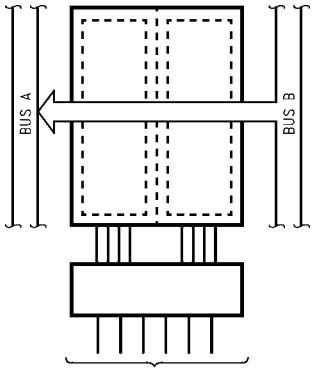
Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both. The select (SAB_n, SBA_n) controls can multiplex stored and real-time. The examples shown below demonstrate the four fundamental bus-management functions that can be performed.

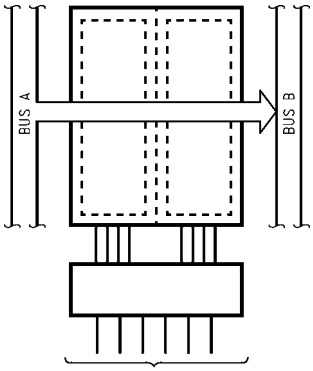
The direction control (DIR_n) determines which bus will receive data when $\overline{OE}_n$ is LOW. In the isolation mode ($\overline{OE}_n$ HIGH), A data may be stored in one register and/or B data may be stored in the other register. When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two busses, A or B, may be driven at a time.

Real-Time Transfer
Bus B to Bus A



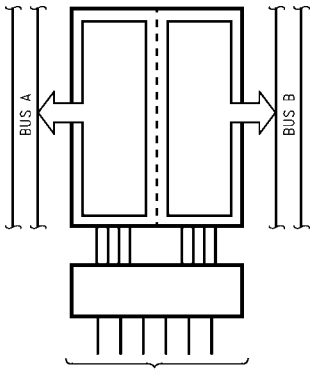
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Real-Time Transfer
Bus A to Bus B



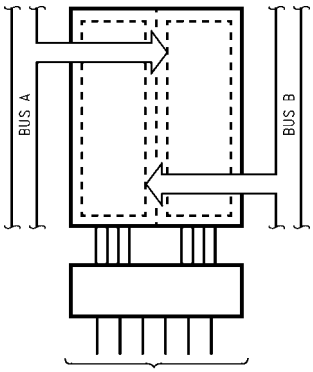
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	X	X	L	X

Transfer Storage
Data to A or B



$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	H or L	X	H
L	H	H or L	X	H	X

Storage



$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	↑	X	L	X
L	X	X	↑	X	L
H	X	↑	X	X	X
H	X	X	↑	X	X

Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 4)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused inputs and I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 6)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	170						ns
t_{PHL}	Propagation Delay	1.5	5.2	1.5	6.0	1.5	6.2	ns
t_{PLH}	Bus to Bus	1.5	5.2	1.5	6.0	1.5	6.2	
t_{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PLH}	Clock to Bus	1.5	6.0	1.5	7.0	1.5	7.2	
t_{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t_{PLH}	Select to Bus	1.5	6.0	1.5	7.0	1.5	7.2	
t_{PZL}	Output Enable Time	1.5	7.5	1.5	8.5	1.5	9.8	ns
t_{PZH}		1.5	7.5	1.5	8.5	1.5	9.8	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.5	1.5	7.8	
t_S	Setup Time	2.5		2.5		3.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew (Note 7)		1.0					ns
t_{OSLH}			1.0					

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, F = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

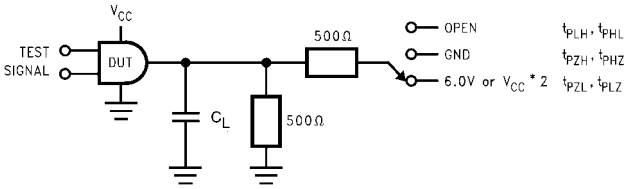
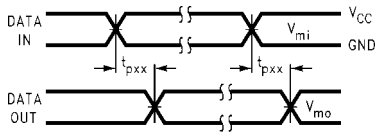
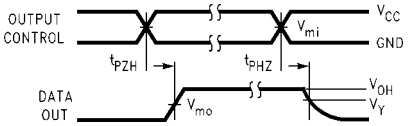


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

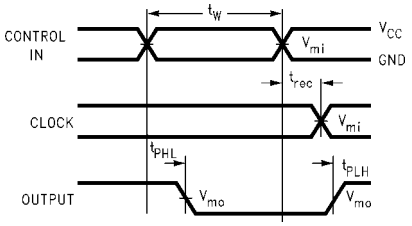
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



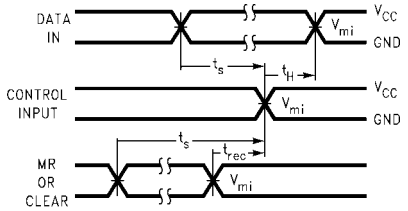
Waveform for Inverting and Non-Inverting Functions



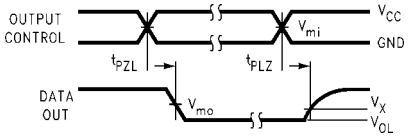
3-STATE Output High Enable and Disable Times for Logic



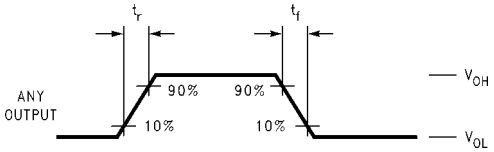
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

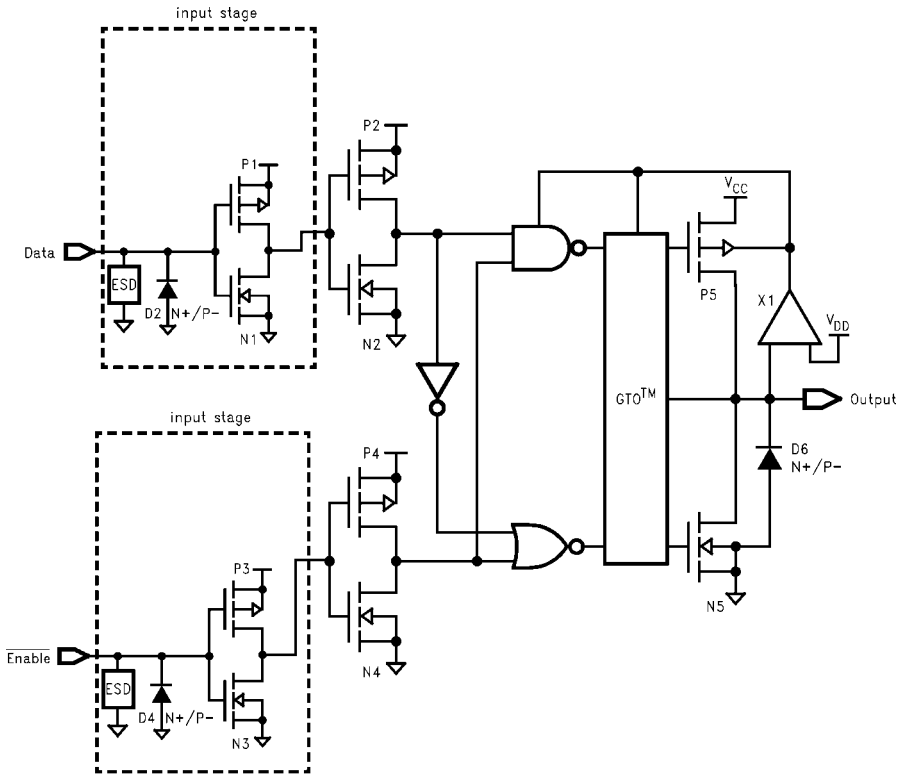


t_{rise} and t_{fall}

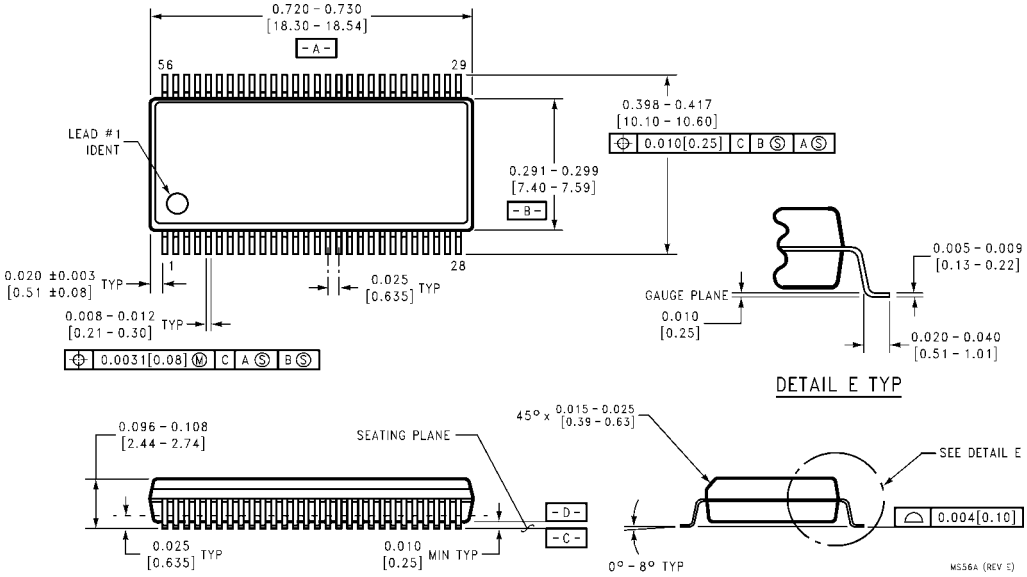
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

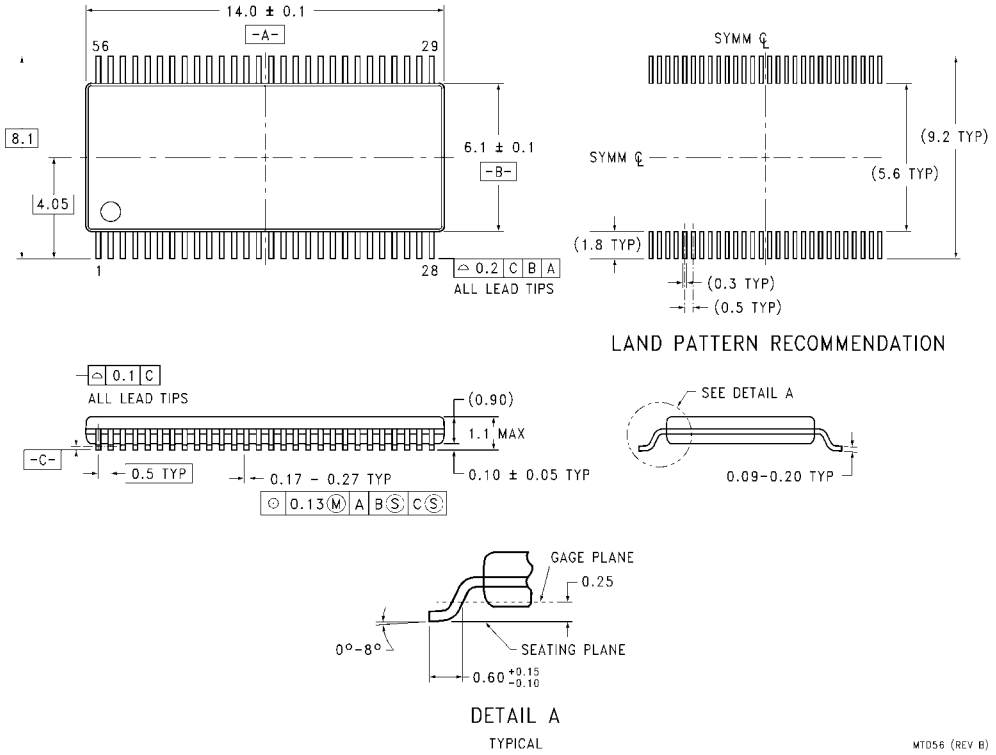


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX16652
Low Voltage Transceiver/Register with 5V Tolerant Inputs and Outputs

General Description

The LCX16652 contains sixteen non-inverting bidirectional bus transceivers with 3-STATE outputs providing multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to the HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function (see Functional Description).

The LCX16652 is designed for low-voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16652 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.7 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

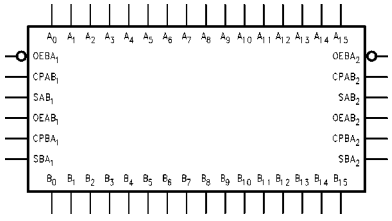
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} and OE tied to GND through a resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16652MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16652MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

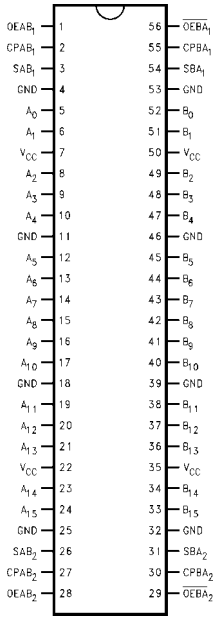
Logic Symbol



Pin Descriptions

Pin Names	Description
A_0–A_{15}	Data Register A Inputs/3-STATE Outputs
B_0–B_{15}	Data Register B Inputs/3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
$OEAB_n$, $\overline{OEBA_n}$	Output Enable Inputs

Connection Diagram



Truth Table

(Note 2)

Inputs						Inputs/Outputs		Operating Mode
OEAB	**$\overline{OEBA}_1$**	**$CPAB_1$**	**$CPBA_1$**	**SAB_1**	**SBA_1**	**A_0 thru A_7**	**B_0 thru B_7**	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Note 2: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs. This also applies to data I/O (A and B: 8–15) and #2 control pins.

Functional Description

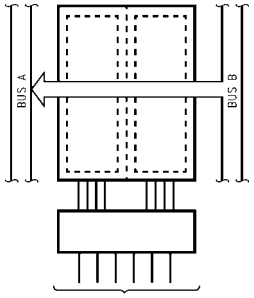
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB_n, SBA_n) controls can multiplex stored and real-time.

The examples below demonstrate the four fundamental bus-management functions that can be performed with the 74LCX16652.

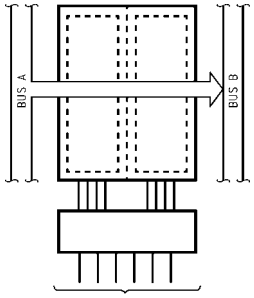
Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW-to-HIGH transitions at the appropriate Clock Inputs ($CPAB_n$, $CPBA_n$) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling $OEAB_n$ and $\overline{OEBA}_n$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Real-Time
Transfer Bus B to Bus A



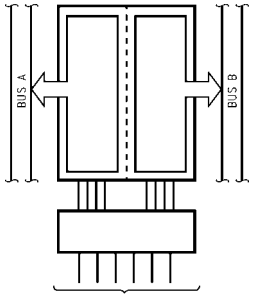
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
L	L	X	X	X	L

Real-Time
Transfer Bus A to Bus B



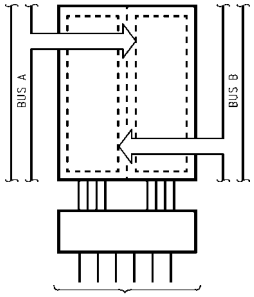
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
H	H	X	X	L	X

Transfer Storage
Data to A or B



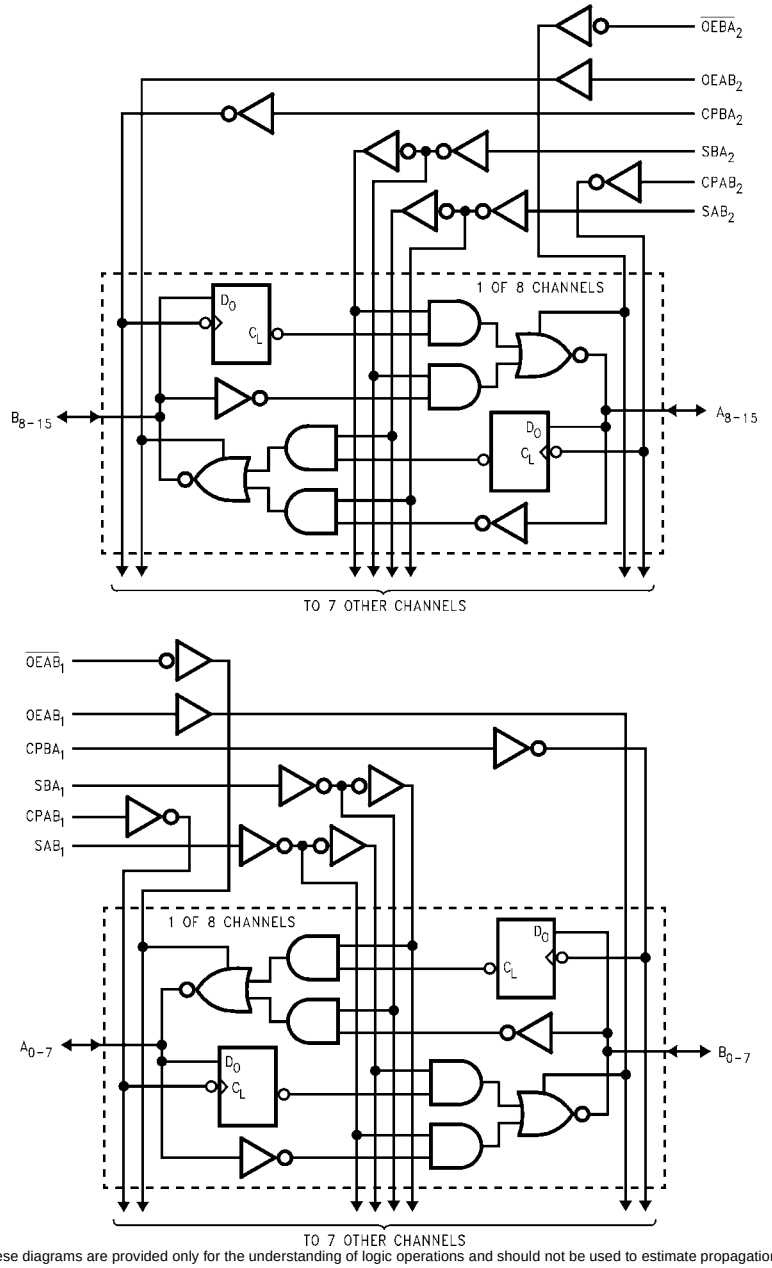
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
H	L	H or L	H or L	H	H

Storage



$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
X	H	⌐	X	X	X
L	X	X	⌐	X	X
L	H	⌐	⌐	X	X

Logic Diagram



Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 4)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 6)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	170						MHz
t_{PHL}	Propagation Delay	1.5	5.7	1.5	6.2	1.5	6.8	ns
t_{PLH}	Bus to Bus	1.5	5.7	1.5	6.2	1.5	6.8	
t_{PHL}	Propagation Delay	1.5	6.2	1.5	7.0	1.5	7.4	ns
t_{PLH}	Clock to Bus	1.5	6.2	1.5	7.0	1.5	7.4	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PLH}	Select to Bus	1.5	6.5	1.5	7.0	1.5	7.8	
t_{PZL}	Output Enable Time	1.5	7.0	1.5	8.0	1.5	9.1	ns
t_{PZH}		1.5	7.0	1.5	8.0	1.5	9.1	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_S	Setup Time	2.5		2.5		3.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.0		3.0		3.5		ns
t_{OSHL}	Output to Output Skew (Note 7)		1.0					ns
t_{OSLH}			1.0					

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

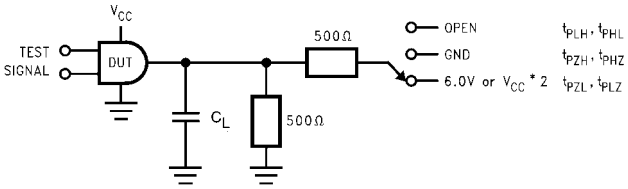
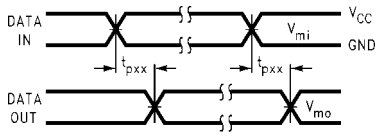
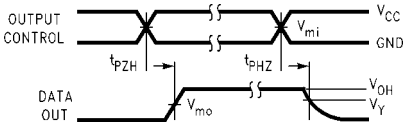


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

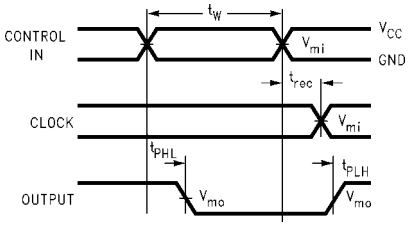
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



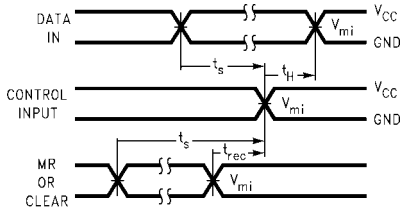
Waveform for Inverting and Non-Inverting Functions



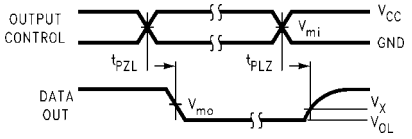
3-STATE Output High Enable and Disable Times for Logic



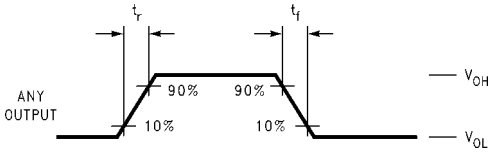
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

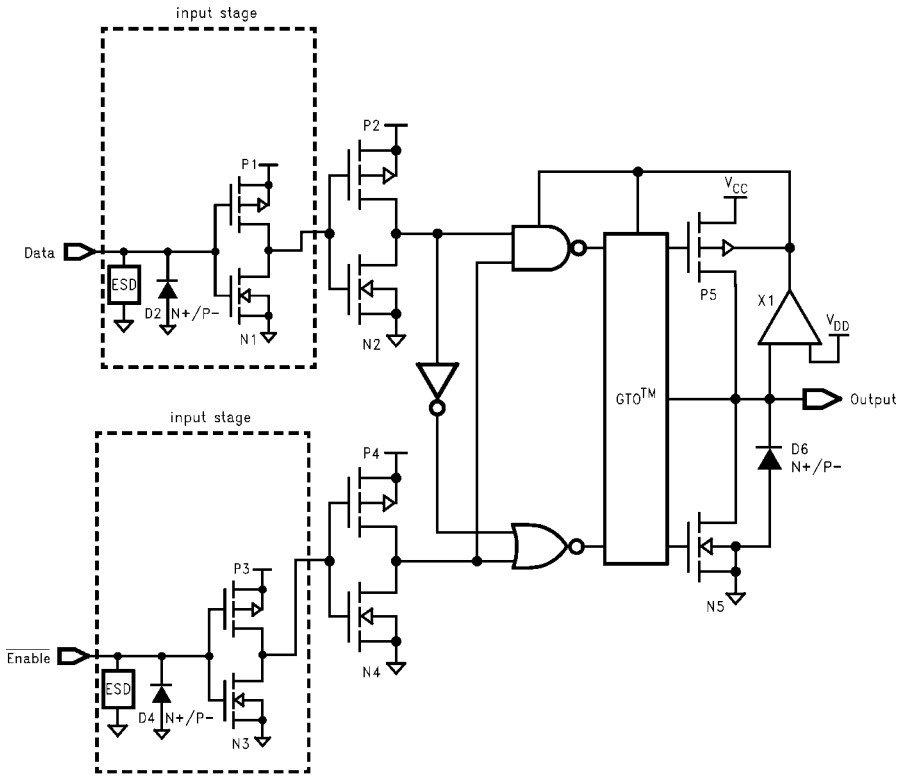


t_{rise} and t_{fall}

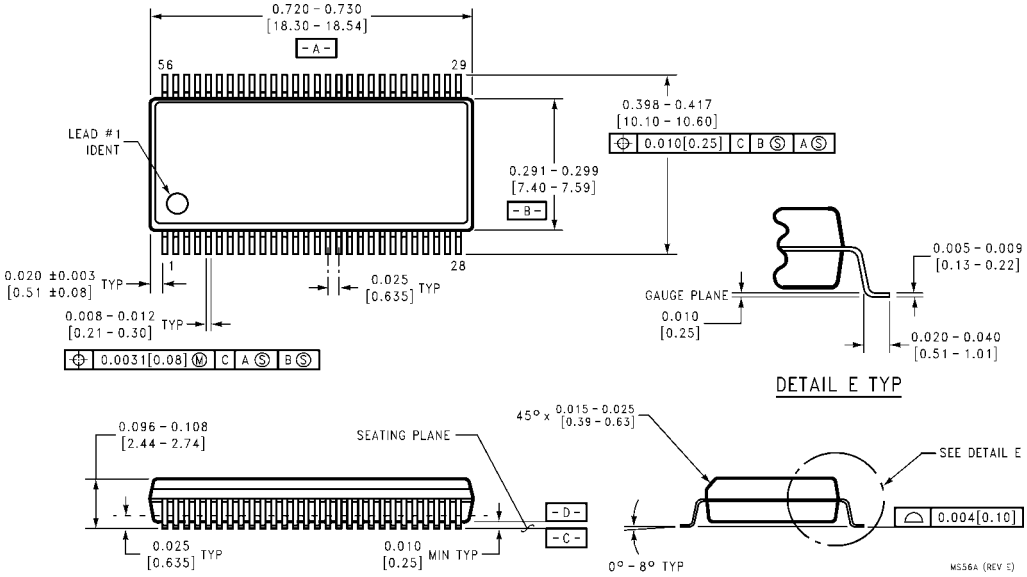
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

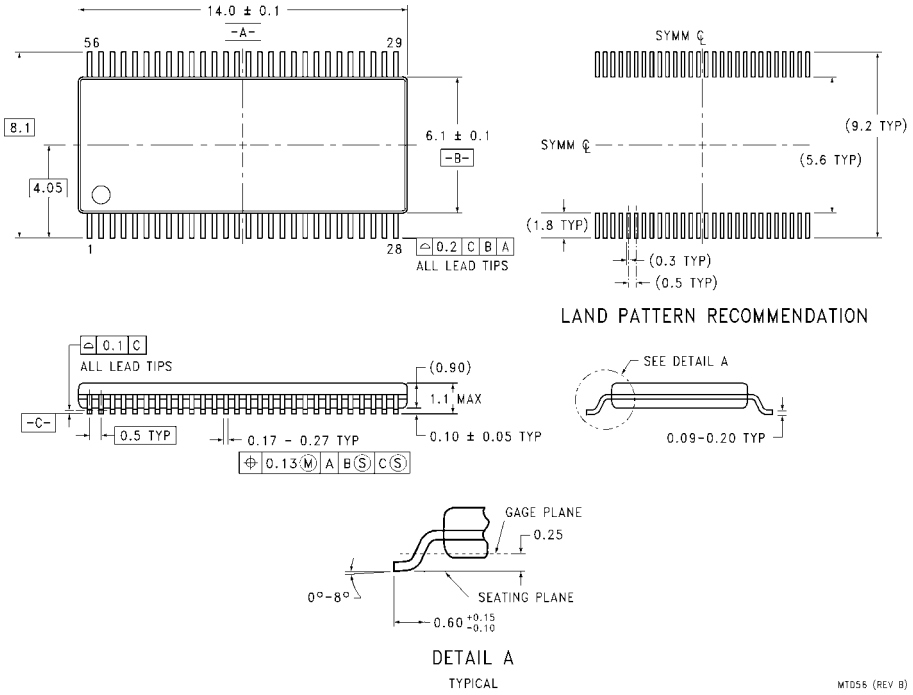


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1996
Revised April 1999

74LCX16821

Low Voltage 20-Bit D-Type Flip-Flop with 5V Tolerant Inputs and Outputs

General Description

The LCX16821 contains twenty non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16821 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.2 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

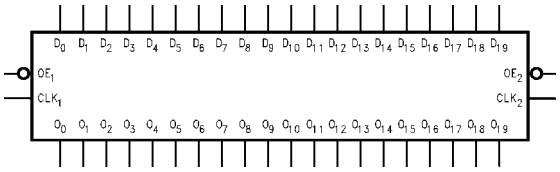
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16821MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16821MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

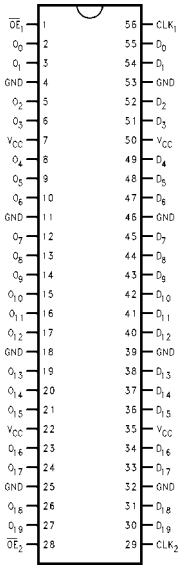
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CLK_n	Clock Input
D_0–D_{19}	Inputs
O_0–O_{19}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
CLK_1	$\overline{OE}_1$	D_0–D_9	O_0–O_9
X	H	X	Z
⌐	L	L	L
⌐	L	H	H
L or H	L	X	O_0

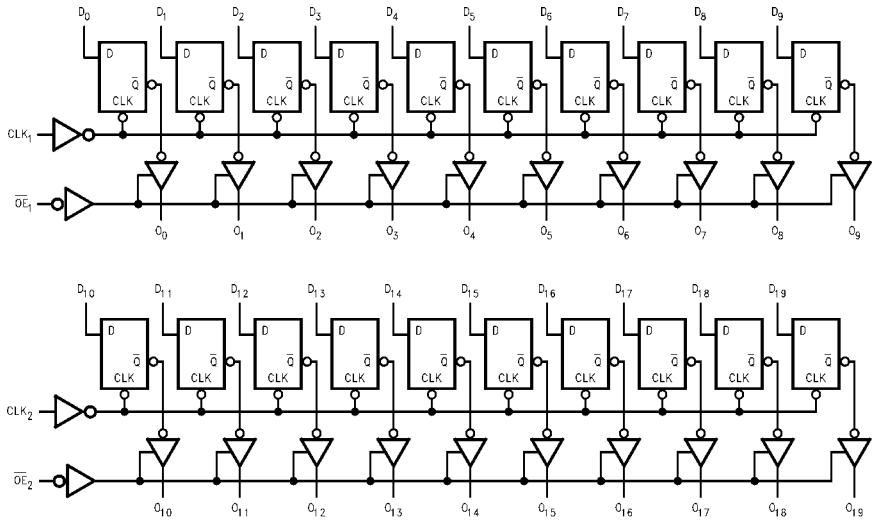
Inputs			Outputs
CLK_2	$\overline{OE}_2$	D_{10}–D_{19}	O_{10}–O_{19}
X	H	X	Z
⌐	L	L	L
⌐	L	H	H
L or H	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
O_0 = Previous O_0 before LOW-to-HIGH transition of Clock
⌐ = LOW-to-HIGH transition

Functional Description

The LCX16821 contains twenty D-type flip-flops with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 20-bit operation. The following description applies to each byte. The twenty flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CLK) transition. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V – 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused pins (Inputs and I/O) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150						MHz
t_{PHL}	Propagation Delay	1.5	6.2	1.5	6.5	1.5	7.4	ns
t_{PLH}	CLK to O_n	1.5	6.2	1.5	6.5	1.5	7.4	
t_{PZL}	Output Enable Time	1.5	6.5	1.5	7.0	1.5	8.5	ns
t_{PZH}		1.5	6.5	1.5	7.0	1.5	8.5	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					
t_S	Setup Time, D_n to CLK	2.5		2.5		3.0		ns
t_H	Hold Time, D_n to CLK	1.5		1.5		2.0		ns
t_W	CLK Pulse Width	3.3		3.3		3.8		ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	1.0	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_O	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

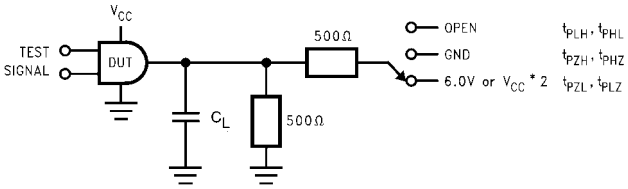
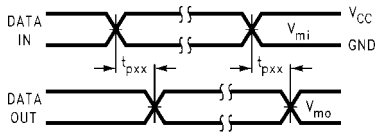
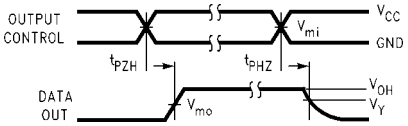


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

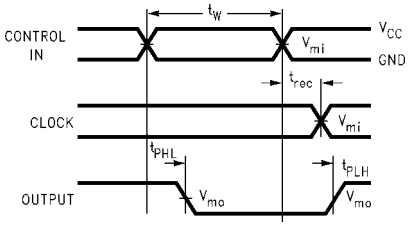
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



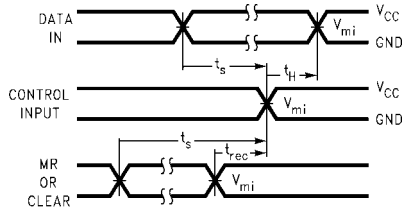
Waveform for Inverting and Non-Inverting Functions



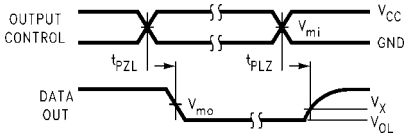
3-STATE Output High Enable and Disable Times for Logic



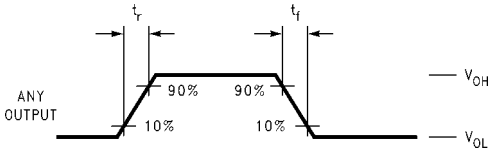
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

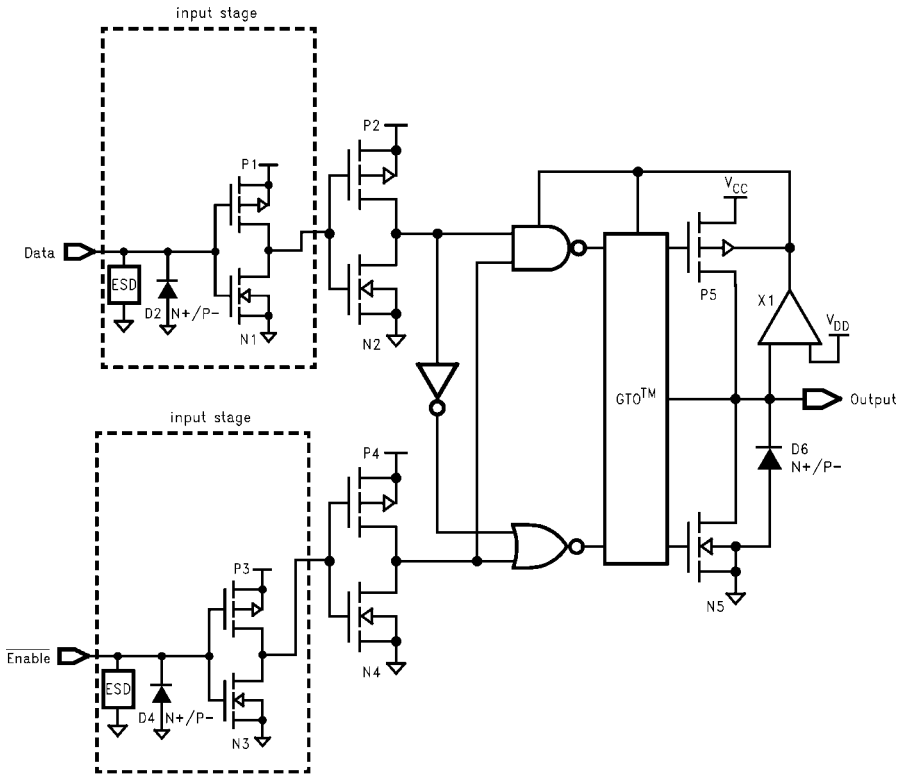


t_{rise} and t_{fall}

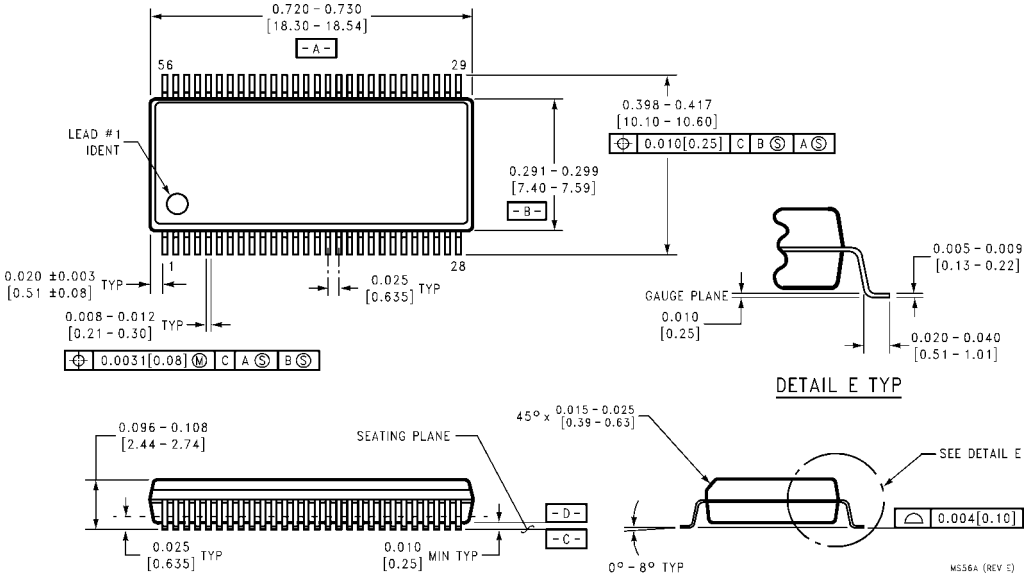
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

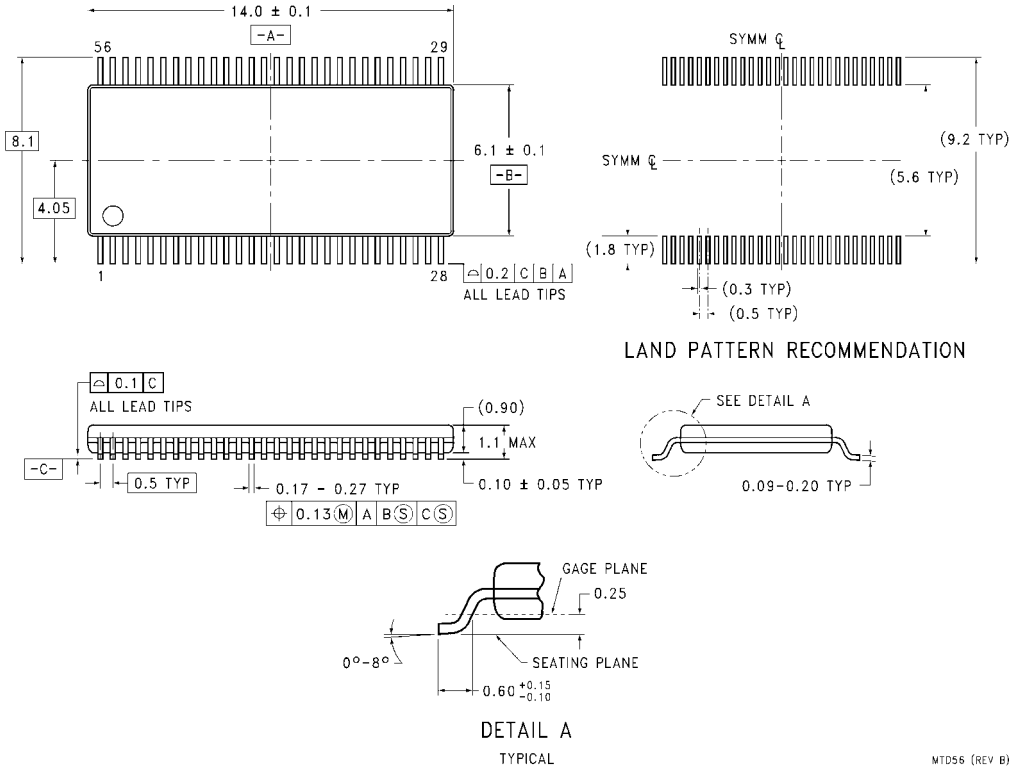


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1995
Revised April 1999

74LCX16841

Low Voltage 20-Bit Transparent Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX16841 contains twenty non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The LCX16841 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16841 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.5 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

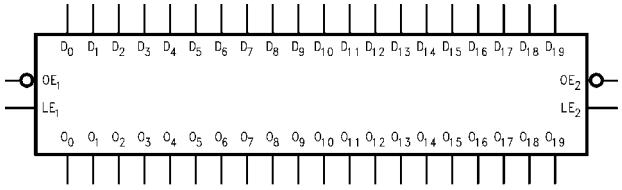
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16841MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16841MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

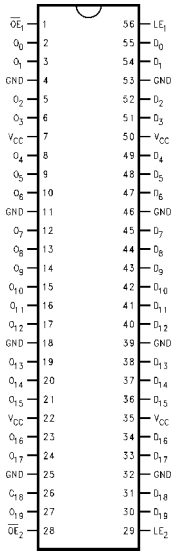
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
D_0–D_{19}	Inputs
O_0–O_{19}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	D_0–D_9	O_0–O_9
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

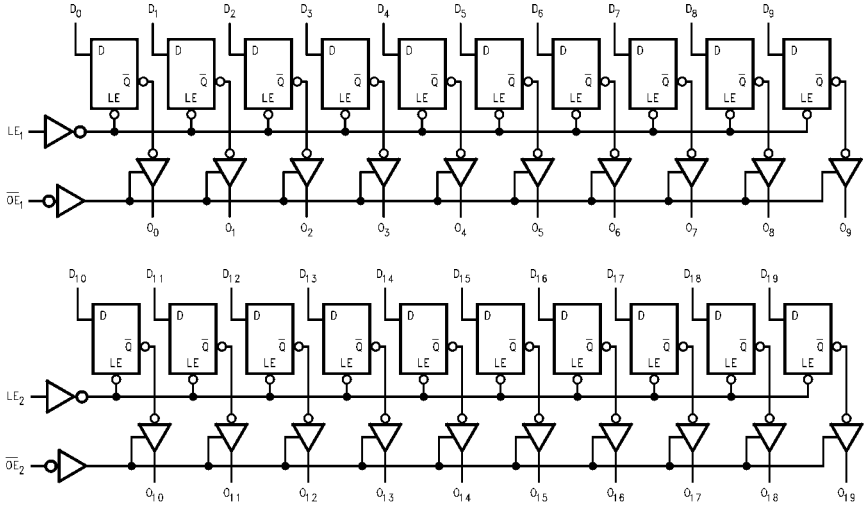
Inputs			Outputs
LE_2	$\overline{OE}_2$	D_{10}–D_{19}	O_{10}–O_{19}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Functional Description

The LCX16841 contains twenty D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 20-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the D_n enters the latches. In this condition the latches are transparent, i.e. a latch output will change states each time its D input changes. When LE_n is LOW, the latches store information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagrams



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.0	1.5	6.6	ns
t_{PLH}	D_n to O_n	1.5	5.5	1.5	6.0	1.5	6.6	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.5	1.5	6.6	ns
t_{PLH}	LE to O_n	1.5	5.5	1.5	6.5	1.5	6.6	
t_{PZL}	Output Enable Time	1.5	6.5	1.5	7.0	1.5	8.5	ns
t_{PZH}		1.5	6.5	1.5	7.0	1.5	8.5	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					
t_S	Setup Time, D_n to LE	2.5		2.5		3.0		ns
t_H	Hold Time, D_n to LE	1.5		1.5		2.0		ns
t_W	LE Pulse Width	3.3		3.3		3.8		ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	−0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_O	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

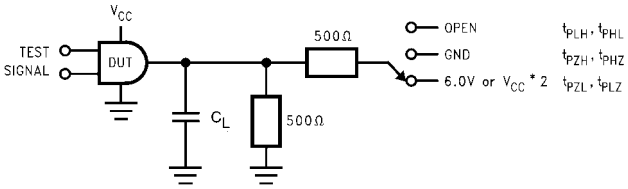
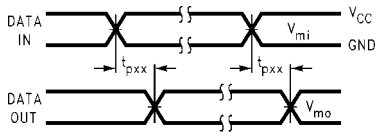
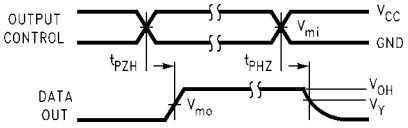


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

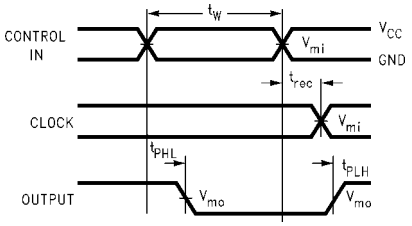
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



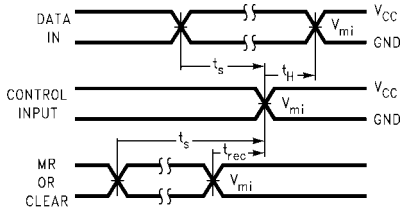
Waveform for Inverting and Non-Inverting Functions



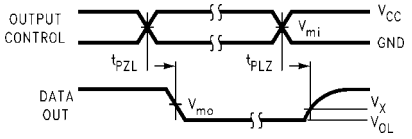
3-STATE Output High Enable and Disable Times for Logic



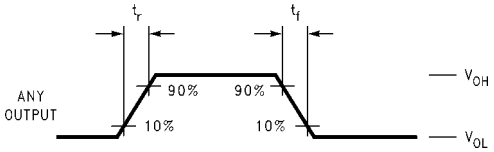
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

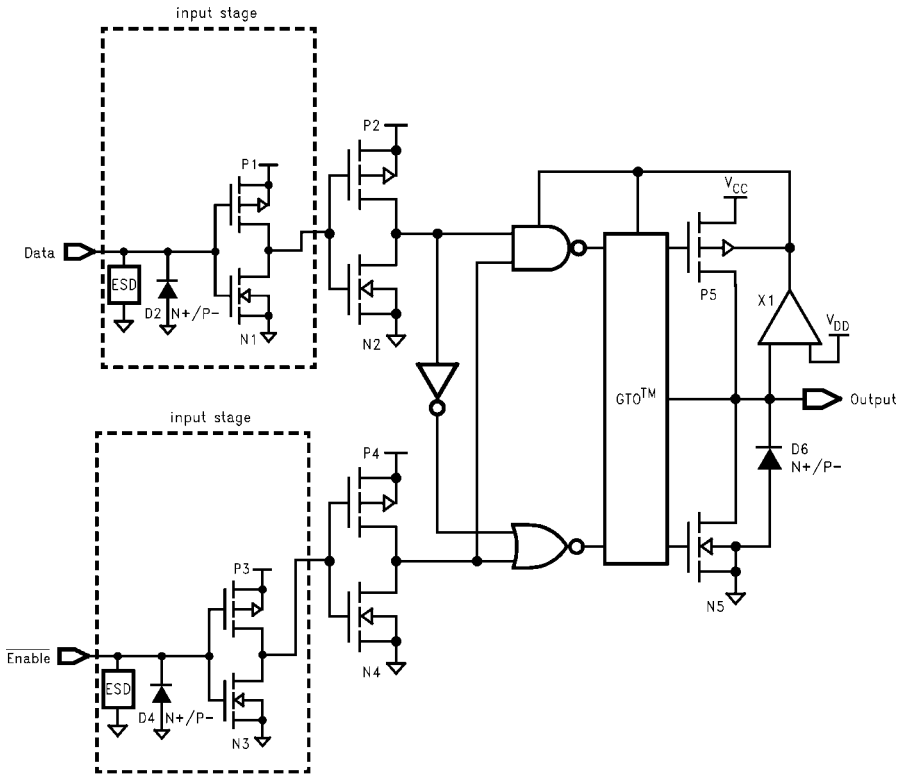


t_{rise} and t_{fall}

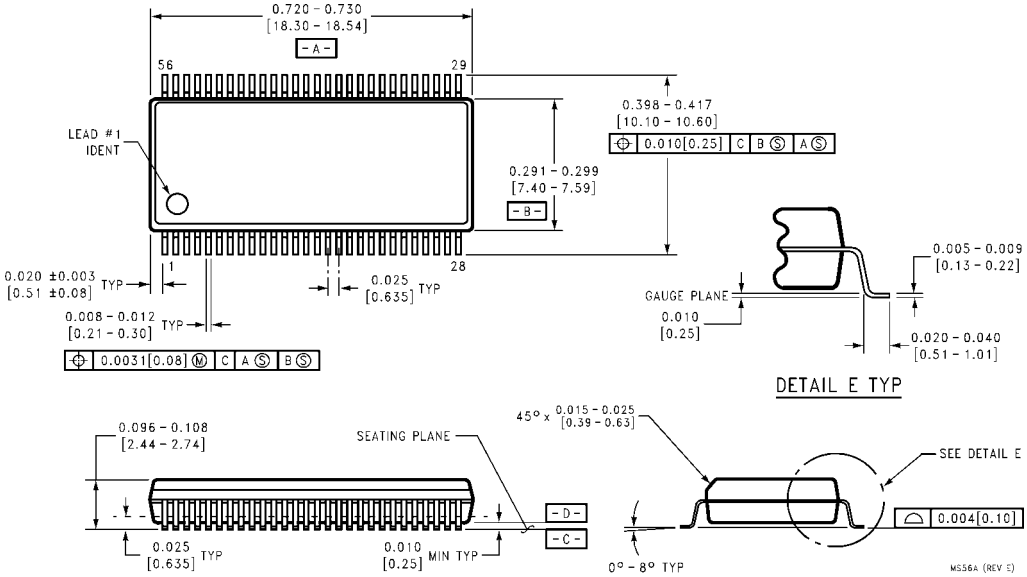
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

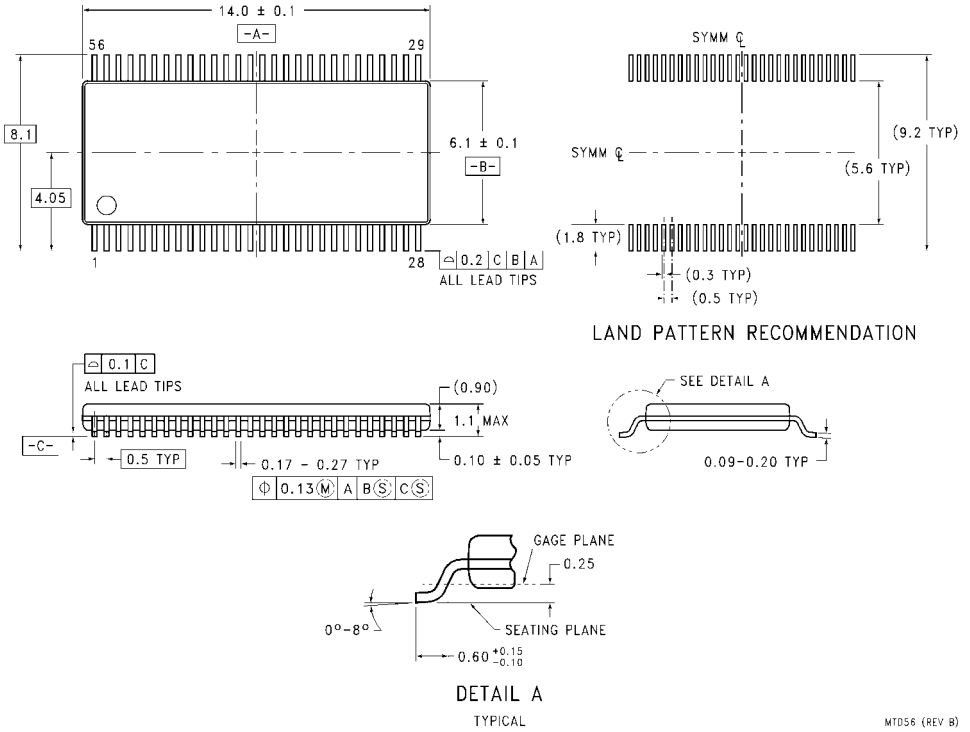


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

October 1995
Revised June 1999

74LCX2244

Low Voltage Buffer/Line Driver with 5V Tolerant Inputs and Outputs with 26Ω Series Resistors in the Outputs

General Description

The LCX2244 contains eight non-inverting buffers with 3-STATE outputs. The device may be employed as a memory address driver, clock driver and bus-oriented transmitter/receiver. The LCX2244 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The 26Ω-series resistors help reduce output overshoot and undershoot.

The LCX2244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.5 ns t_{PD} max (V_{CC} = 3.3V) 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- 26Ω-series resistors in the outputs
- Supports live insertion/withdrawal (Note 1)
- ±12 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

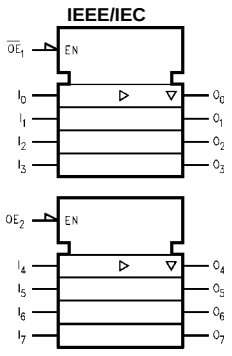
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

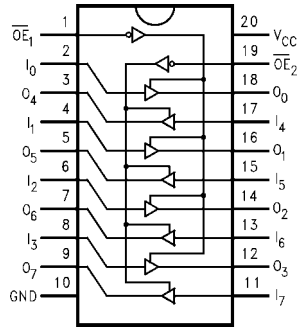
Order Number	Package Number	Package Description
74LCX2244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX2244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX2244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	H	L
L	H	H
H	X	Z

H = HIGH Voltage Level
X = Immaterial
L = LOW Voltage Level
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to +7.0	Output in 3-STATE	V
		–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±12	mA
		V_{CC} = 2.7V – 3.0V		±8	
		V_{CC} = 2.3V – 2.7V		±4	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V – 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = –40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = –4 mA	2.3	1.8		
		I_{OH} = –4 mA	2.7	2.2		
		I_{OH} = –6 mA	3.0	2.4		
		I_{OH} = – 8mA	2.7	2.0		
		I_{OH} = –12 mA	3.0	2.0		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 4 mA	2.3		0.6	
		I_{OL} = 4 mA	2.7		0.4	
		I_{OL} = 6 mA	3.0		0.55	
		I_{OL} = 8 mA	2.7		0.6	
		I_{OL} = 12 mA	3.0		0.8	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		3.6V ≤ V_I, V_O ≤ 5.5V (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5 \pm 0.2V$		
		$C_L = 50pF$		$C_L = 50pF$		$C_L = 30pF$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PLH}	Data to Output	1.5	7.5	1.5	8.5	1.5	9.0	
t_{PZL}	Output Enable Time	1.5	9.0	1.5	10.0	1.5	10.5	ns
t_{PZH}		1.5	9.0	1.5	10.0	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	8.0	1.5	8.4	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	0.35	V
		C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	0.25	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	–0.35	V
		C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	–0.25	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	7	pF
C_{OUT}	Output Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

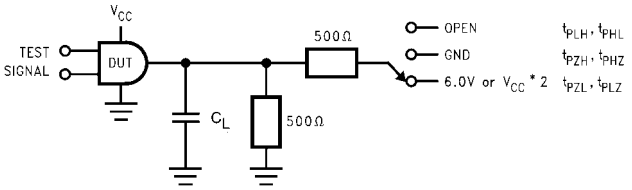
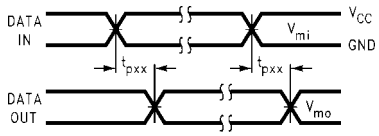
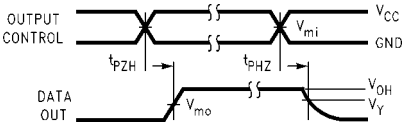


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

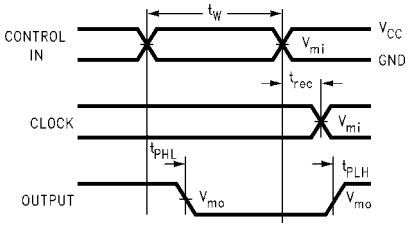
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



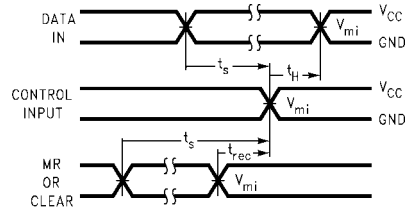
Waveform for Inverting and Non-Inverting Functions



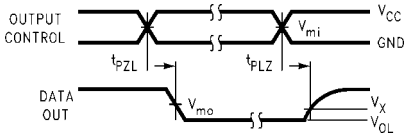
3-STATE Output High Enable and Disable Times for Logic



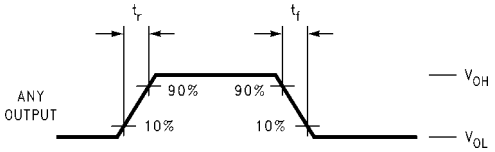
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

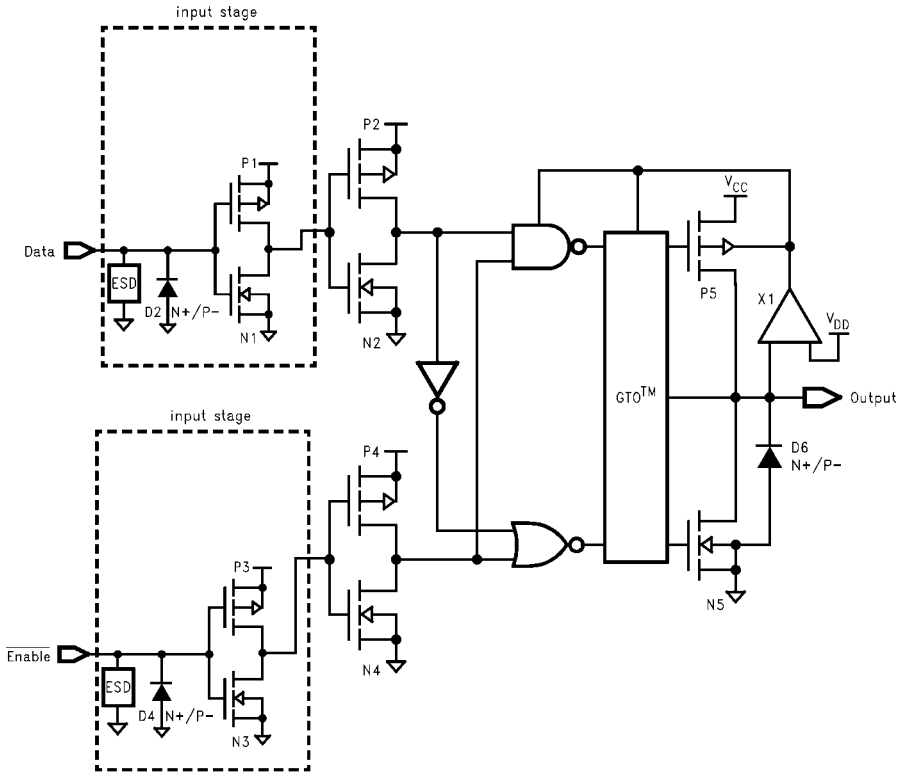


t_{rise} and t_{fall}

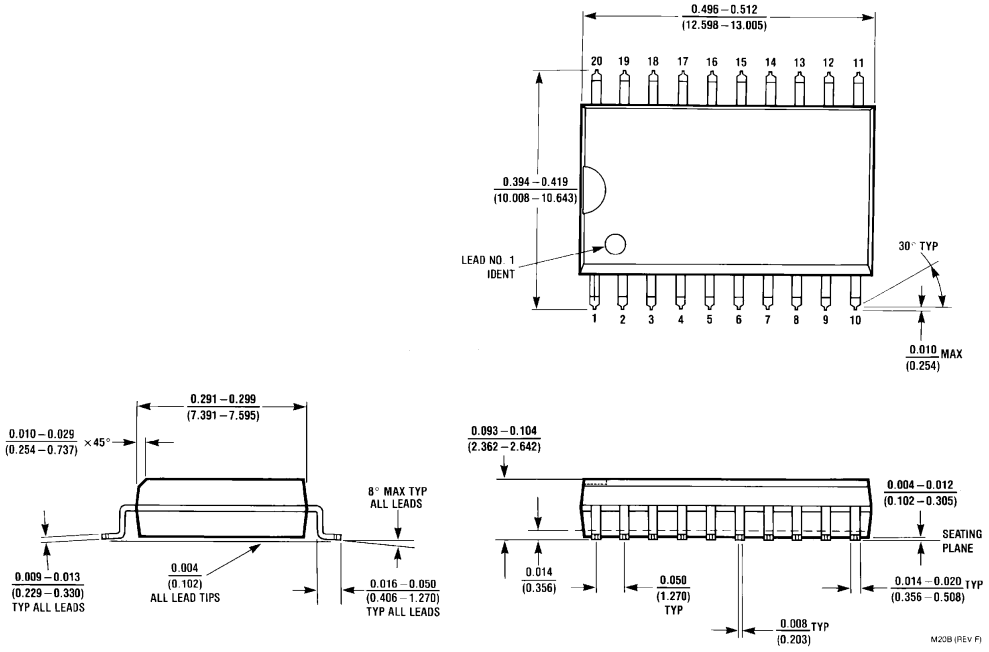
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

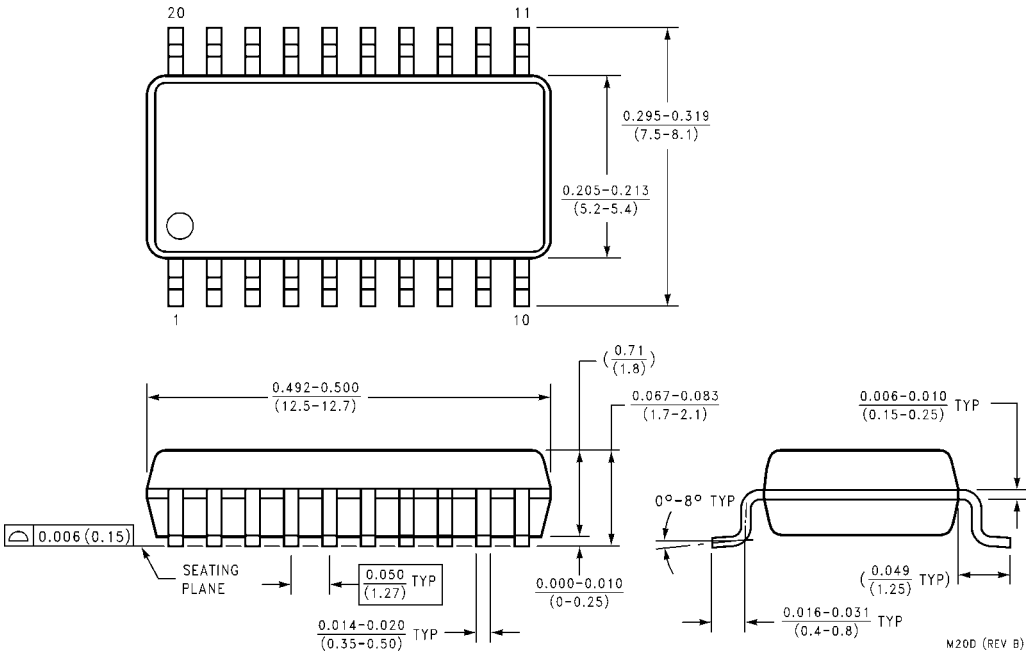
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

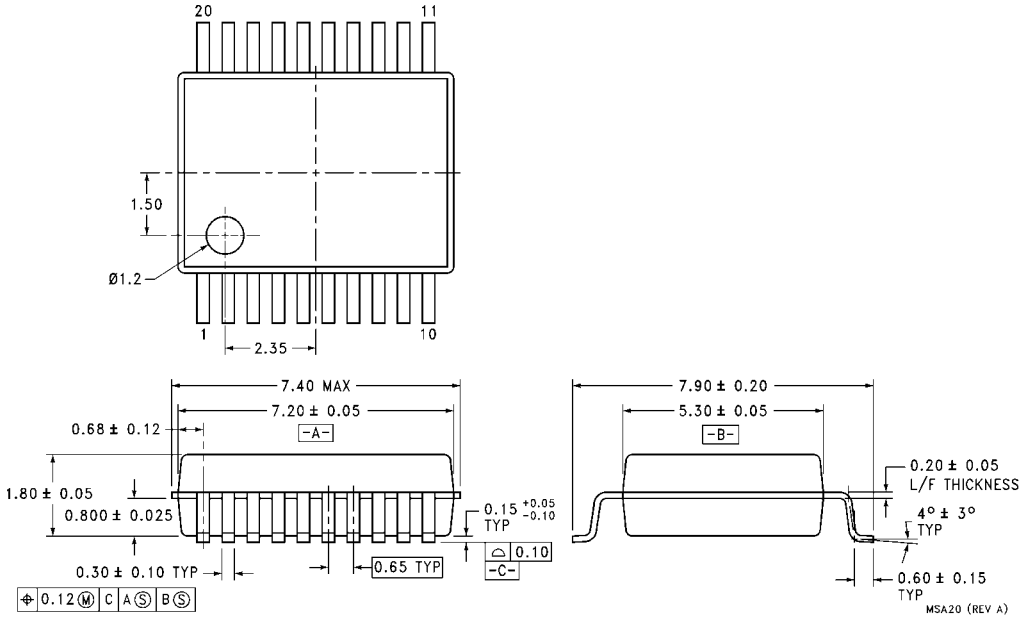


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



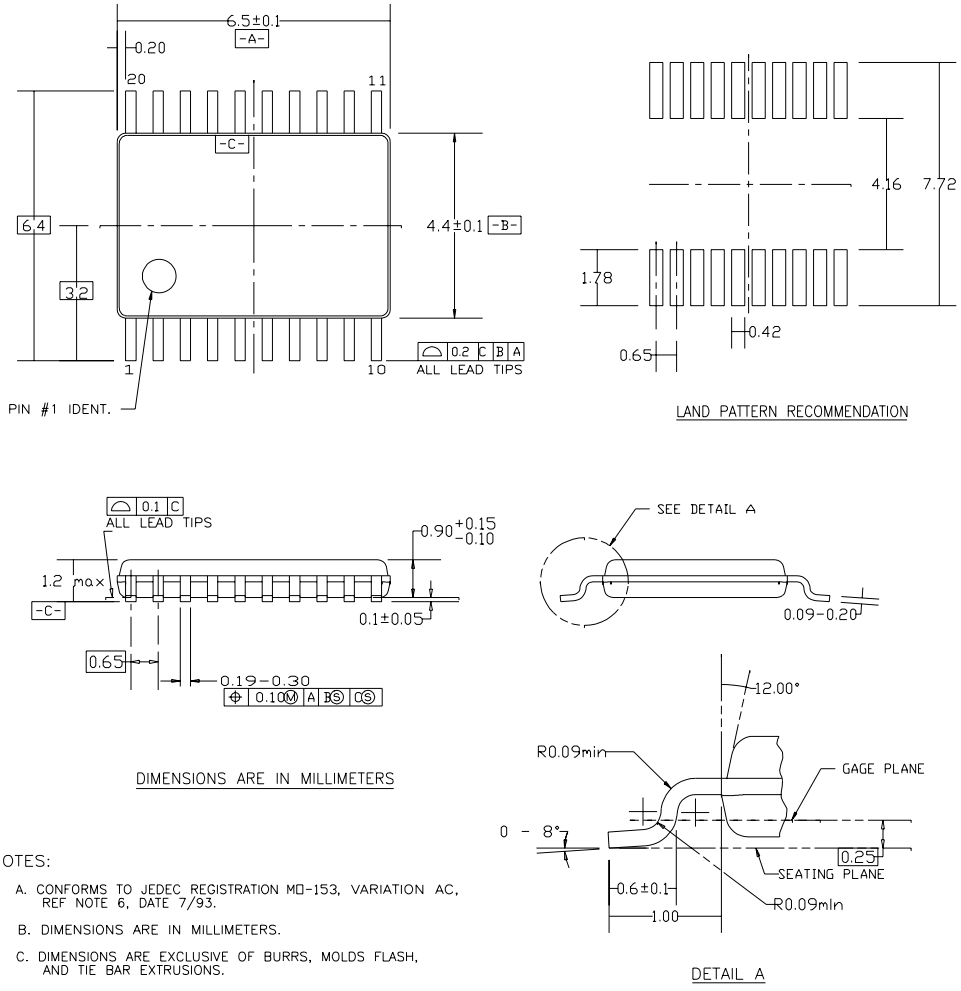
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 43.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR TM

PRELIMINARY
January 1998

74LCXR2245
Low Voltage Bidirectional Transceiver with 5V Tolerant Inputs and Outputs (Preliminary)

General Description

The LCXR2245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The T/$\overline{R}$ input determines the direction of data flow through the device. The $\overline{OE}$ input disables both the A and B ports by placing them in a high impedance state. The 26Ω-series resistor helps reducing output overshoot and undershoot.

The LCXR2245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

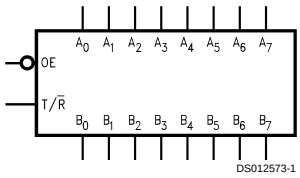
- 5V tolerant inputs and outputs
- 10 µA I_{CCQ} max
- Power down high impedance inputs and outputs
- Equivalent 26Ω-series resistor on all outputs
- Supports live insertion/withdrawal
- 2.0V–3.6V V_{CC} supply operation
- ±12 mA output drive
- Implements patented noise/EMI reduction circuitry
- Functionally compatible with the 74 series 245
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 200V

Ordering Code: See

Order Number	Package Number	Package Description
74LCXR2245WM	M20B	20-Lead (0.300" Wide) Small Outline Integrated Circuit, SOIC, JEDEC
74LCXR2245SJ	M20D	20-Lead Molded Small Outline Package, SOIC,EIAJ
74LCXR2245MSA	MSA20	20-Lead Molded Shrink Small Outline Package, EIAJ, Type II
74LCXR2245MTC	MTC20	20-Lead Thin Shrink Small Outline Package, TSSOP

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

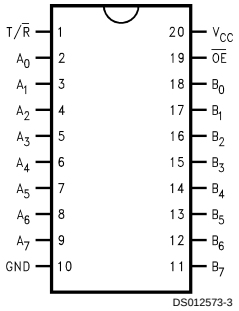
Logic Symbol



DS012573-1

Connection Diagram

Pin Assignment for SOIC, SSOP and TSSOP



DS012573-3

Pin Descriptions

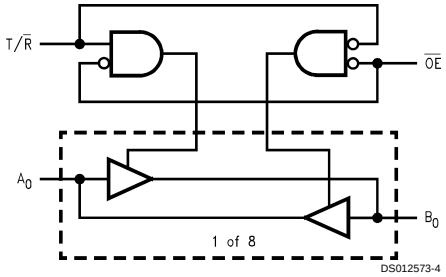
Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B_O–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–B_7 Data to Bus B_0–B_7
H	X	High Z STATE on A_0–A_7, B_0–B_7

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in High or Low State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		˚C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±12	mA
		V_{CC} = 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	˚C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40˚C to +85˚C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −4 mA	2.7	2.2		V
		I_{OH} = −6 mA	3.0	2.4		V
		I_{OH} = −8 mA	2.7	2.0		V
		I_{OH} = −12 mA	3.0	2.0		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 4 mA	2.7		0.4	V
		I_{OL} = 6 mA	3.0		0.55	V
		I_{OL} = 8 mA	2.7		0.6	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V	2.7–3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		10	µA
		3.6V ≤ V_I, V_O ≤ 5.5V	2.7–3.6		±10	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40^\circ C$ to $+85^\circ$ CL = 50pF, RL = 500Ω				Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
		Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	7.0	1.5	8.0	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	
t_{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	ns
t_{PHZ}		1.5	7.5	1.5	8.5	
t_{OSHL},	Output to Output Skew		1.0			ns
t_{OSLH}	(Note 4)		1.0			

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

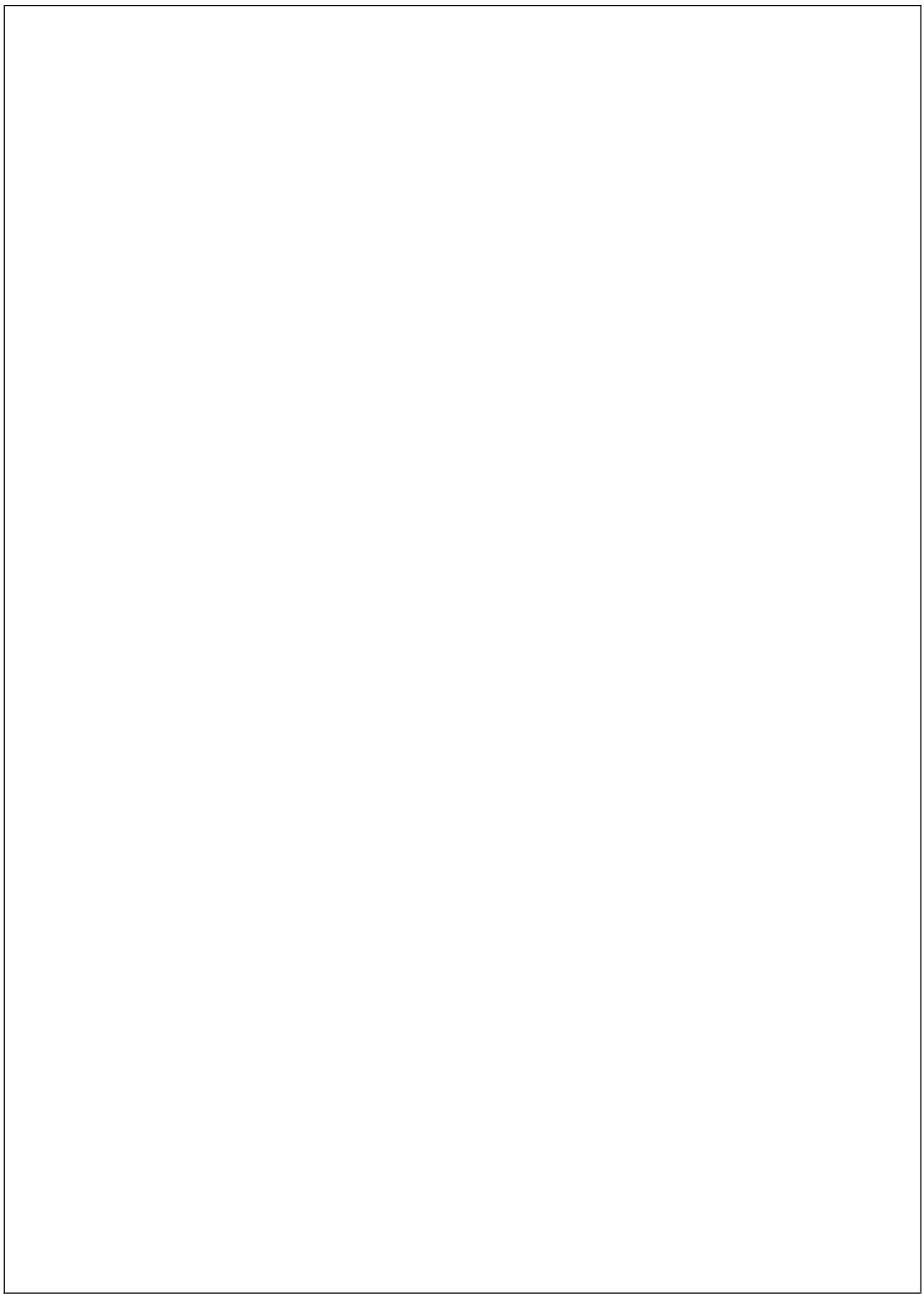
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25^\circ C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	−0.8	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC}, F = 10 MHz	25	pF

Book Extract End



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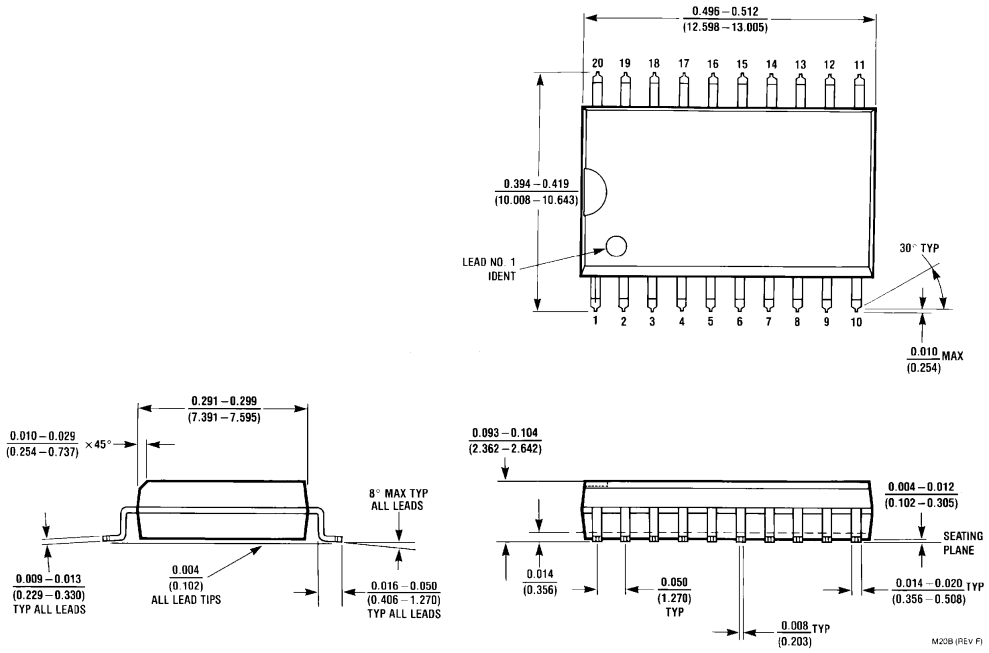
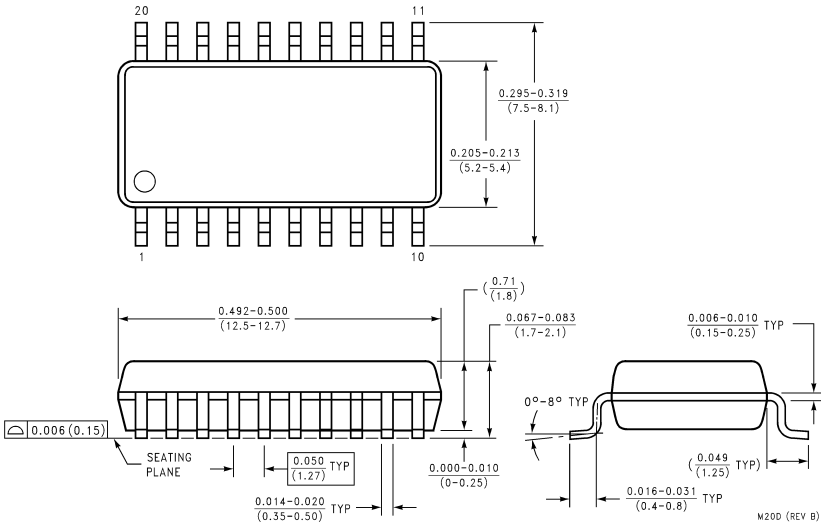
Physical Dimensions inches (millimeters) unless otherwise noted

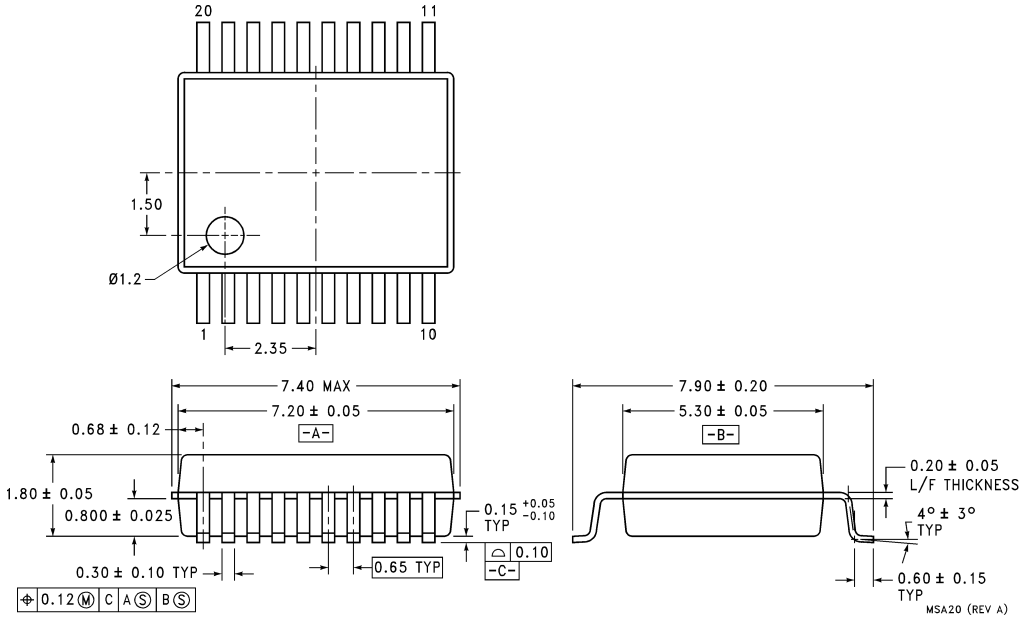


20-Lead (0.300" Wide) Molded Small Outline Package, JEDEC
Package Number M20B



20-Lead (0.300" Wide) Molded Small Outline Package, EIAJ
Package Number M20D

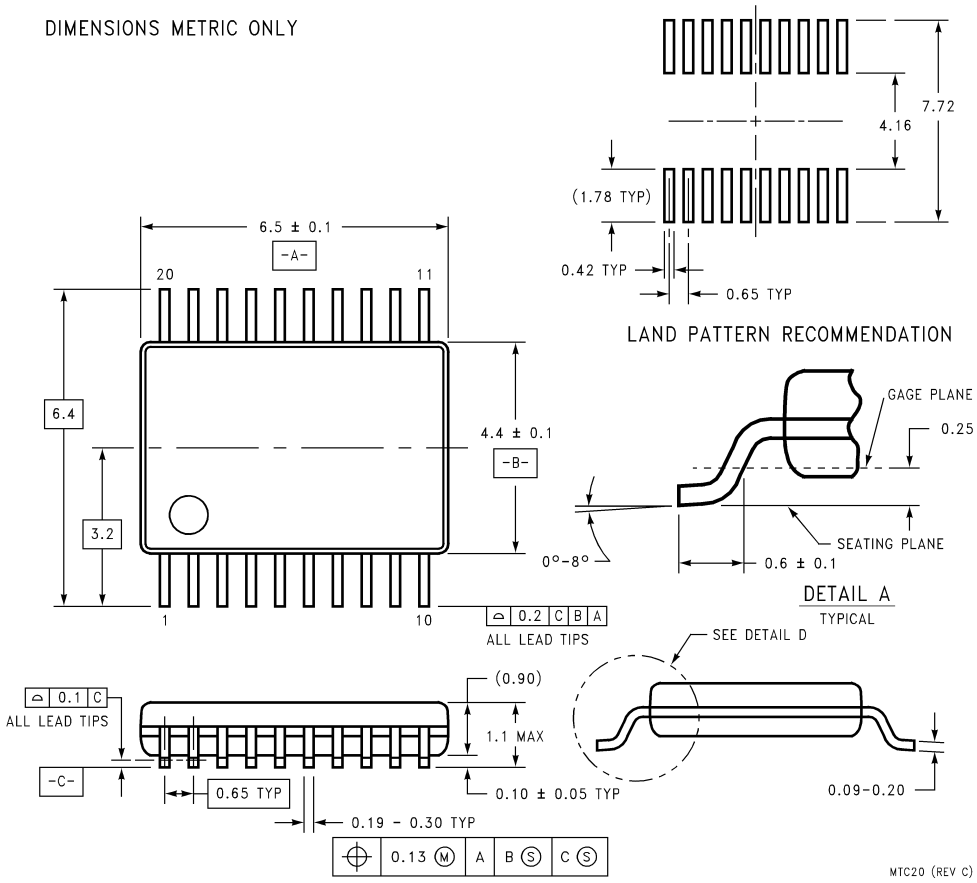
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Molded Shrink Small Outline Package, EIAJ, Type II
Package Number MSA20

PrintDate=1998/01/29 PrintTime=11:35:25 30877 ds012573 Rev. No. 3 cmserv **Proof**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Thin Shrink Small Outline Package, JEDEC
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX240
Low Voltage Octal Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

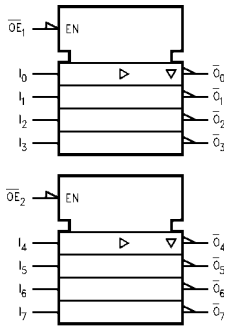
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

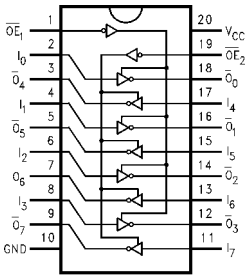
Order Number	Package Number	Package Description
74LCX240WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX240MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Diagram



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V			10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I, V_O ≤ 5.5V (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} = 0.6V	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}		1.5	6.5	1.5	7.5	1.5	7.8	
t_{PZL}	Output Enable Time	1.5	8.0	1.5	9.0	1.5	10.0	ns
t_{PZH}		1.5	8.0	1.5	9.0	1.5	10.0	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	8.0	1.5	8.4	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

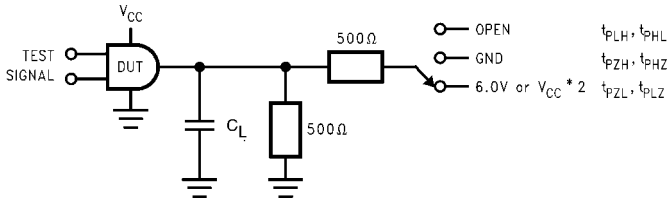
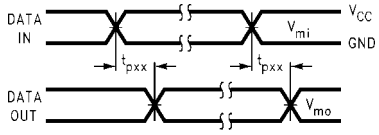
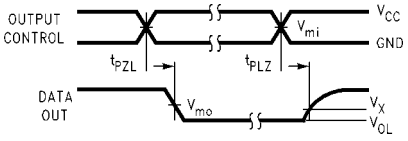


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

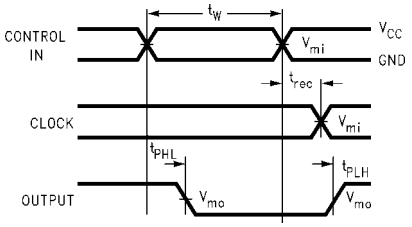
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



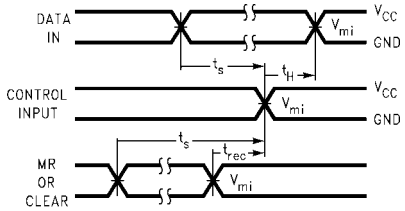
Waveform for Inverting and Non-Inverting Functions



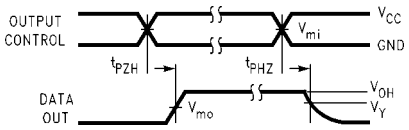
3-STATE Output Low Enable and Disable Times for Logic



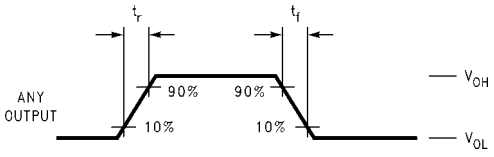
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

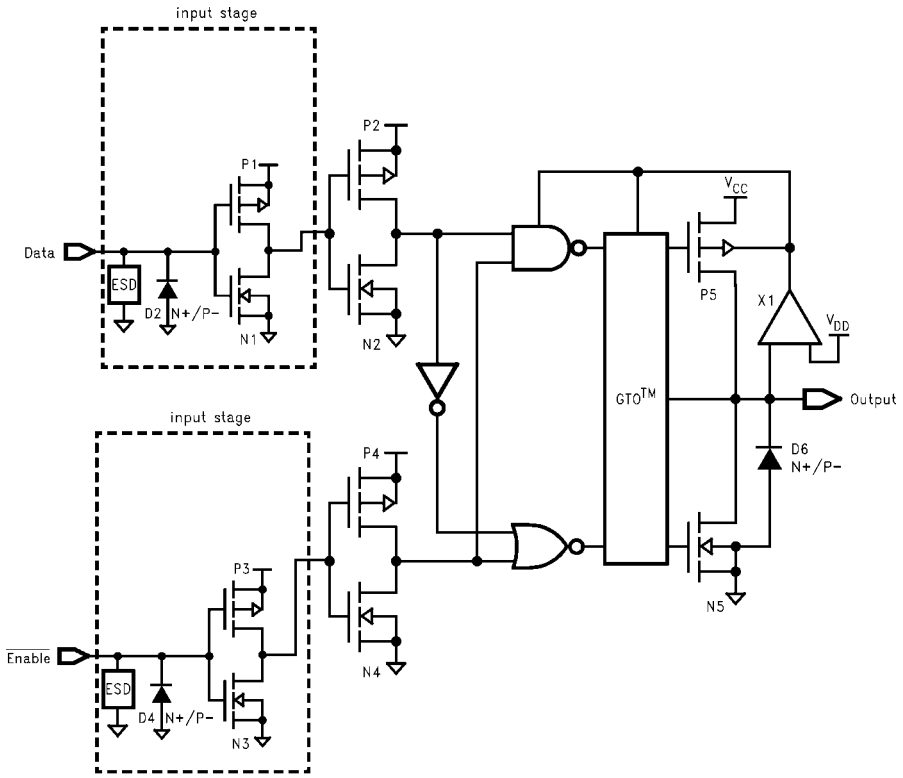


t_{rise} and t_{fall}

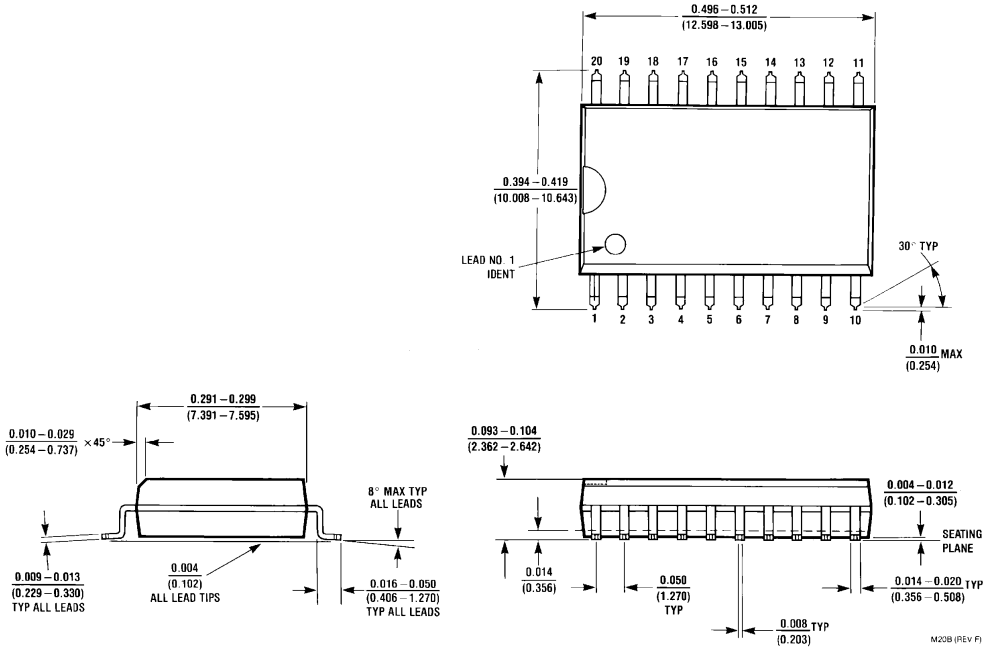
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

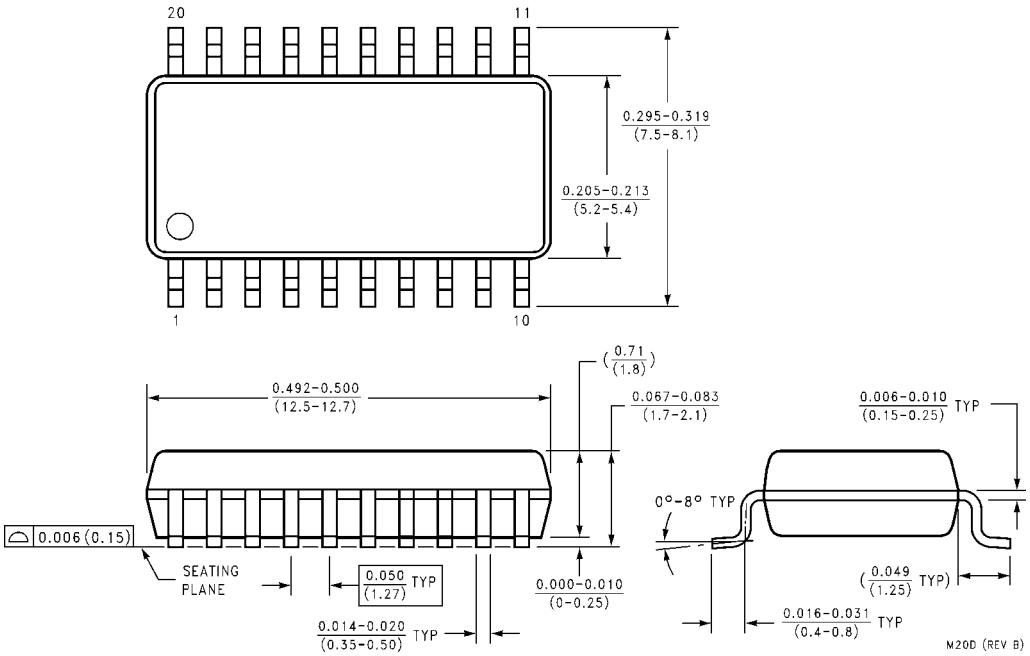
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

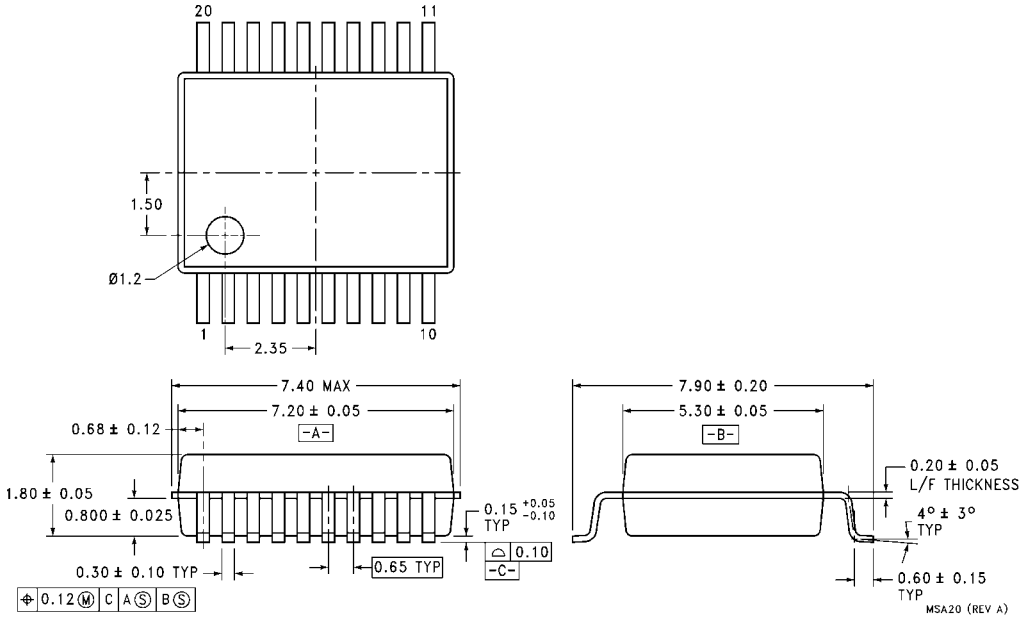


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



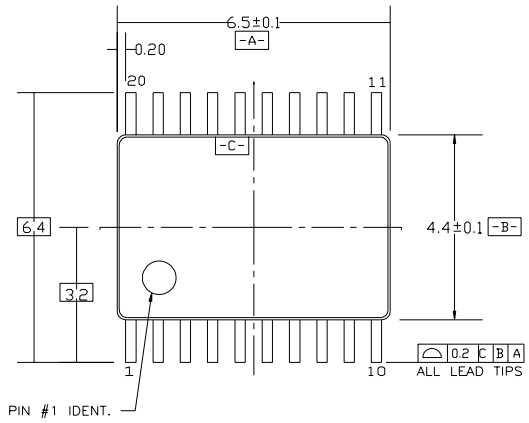
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

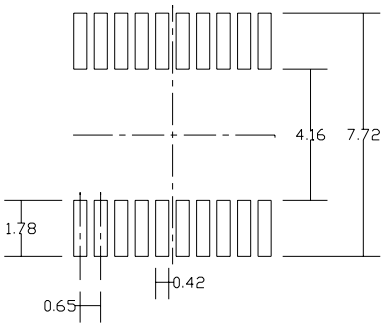
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



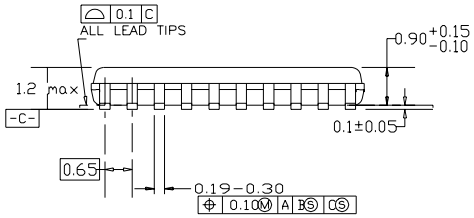
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

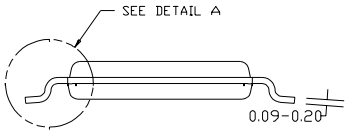
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



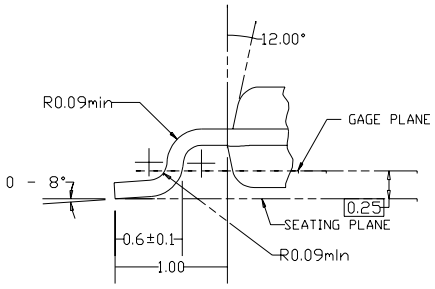


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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August 1998
Revised April 1999

74LCX241
Low Voltage Octal Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX241 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V – 3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human Body Model > 2000V
  - Machine Model > 200V

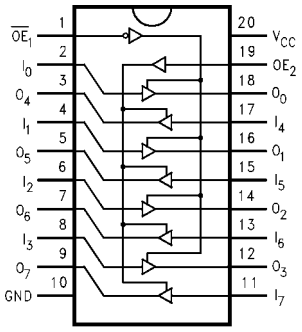
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} and OE should be tied to GND through a resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX241WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX241MSA	M20D	20-Lead Small Outline Package (SOP), EIAJ Type II, 5.3mm Wide
74LCX241SJ	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm WIde
74LCX241MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

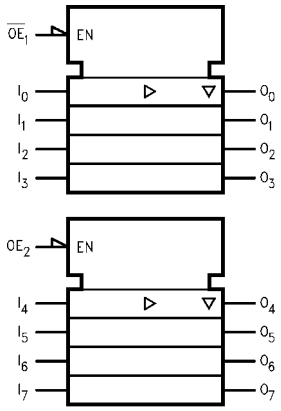
Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, OE_2	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Logic Symbol



Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE_1}$	I_n	
L	L	L
L	H	H
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
OE_2	I_n	
H	H	H
H	L	L
L	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} +0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I< GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O< GND V_O< V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100μA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 - 3.6		±5.0	μA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 - 3.6		±5.0	μA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		10	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 - 3.6		± 10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6v$	2.3 - 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}	Data to Output	1.5	6.5	1.5	7.5	1.5	7.8	
t_{PZL}	Output Enable Time	1.5	8.0	1.5	9.0	1.5	10.0	ns
t_{PZH}		1.5	8.0	1.5	9.0	1.5	10.0	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	8.0	1.5	8.4	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IL} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IL} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	−0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

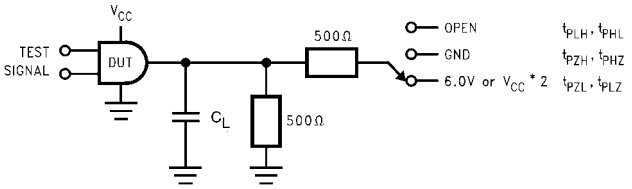
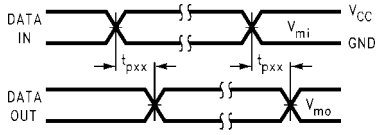
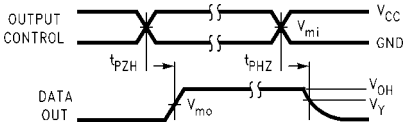


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

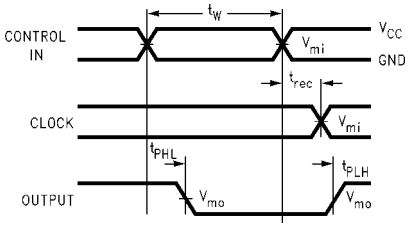
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



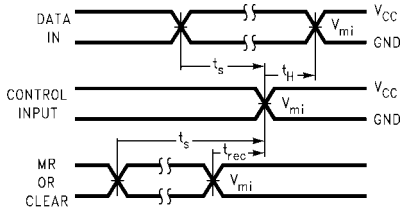
Waveform for Inverting and Non-Inverting Functions



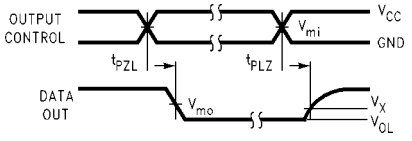
3-STATE Output High Enable and Disable Times for Logic



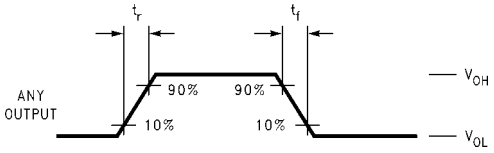
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

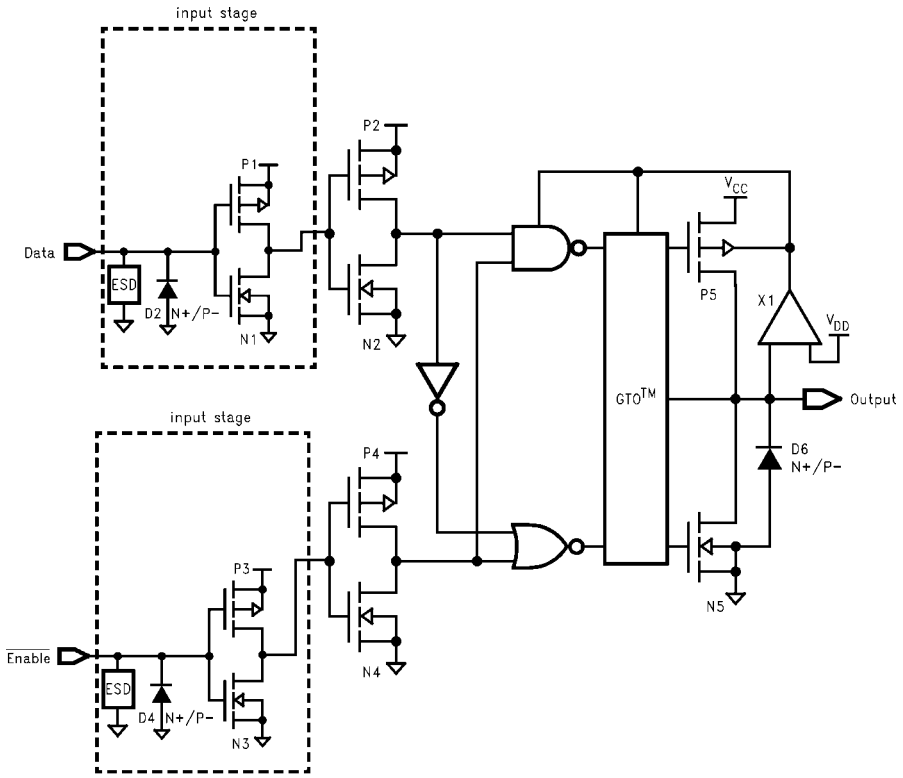


t_{rise} and t_{fall}

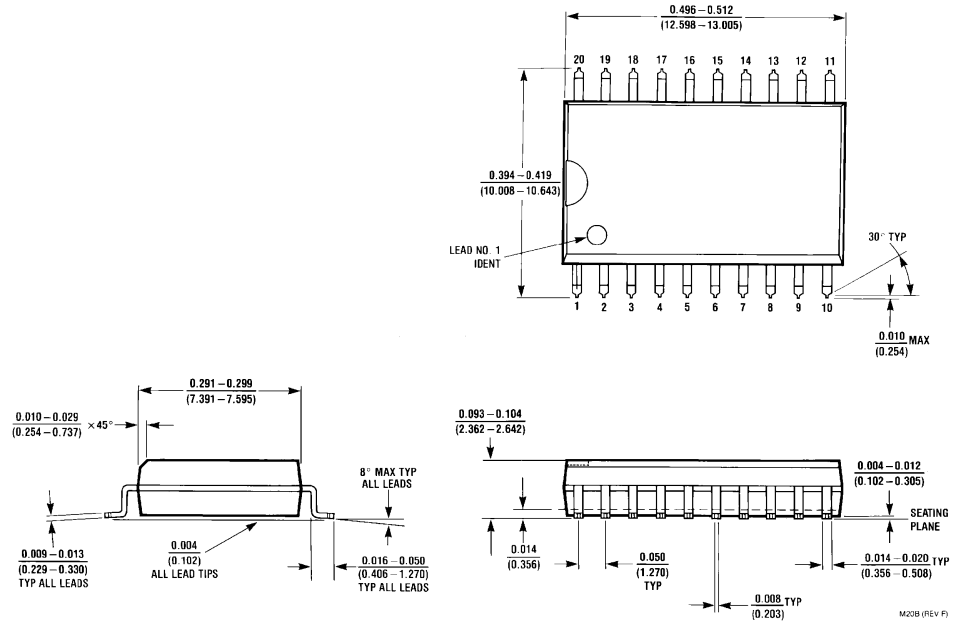
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

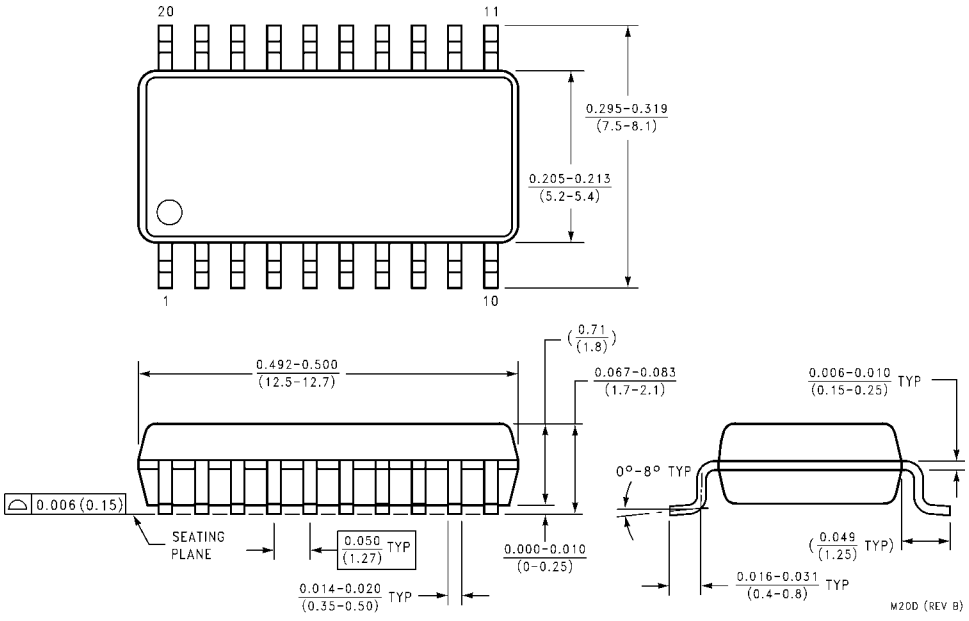
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

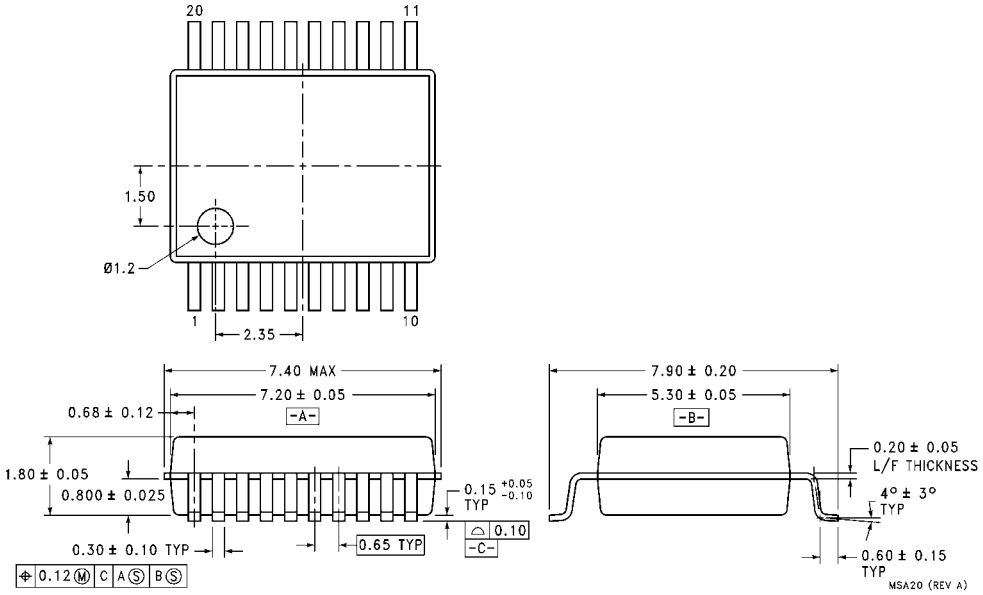


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



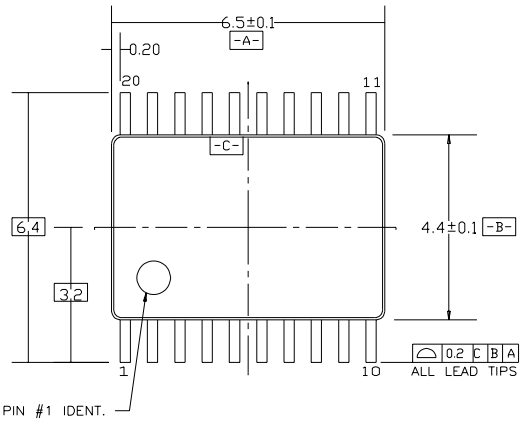
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

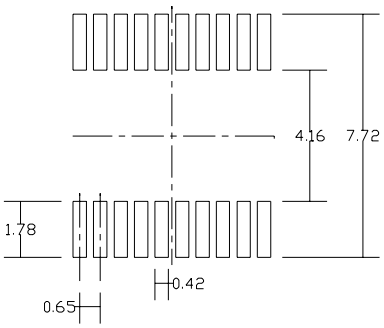
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



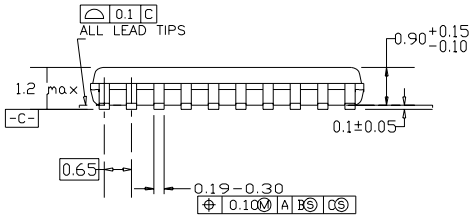
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

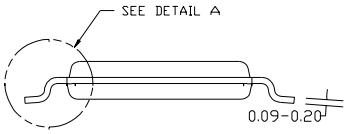


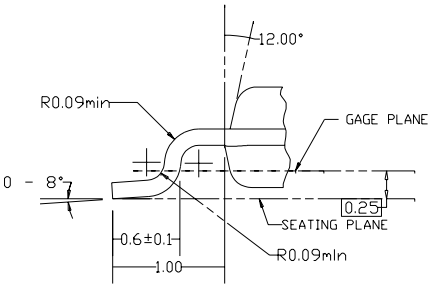


LAND PATTERN RECOMMENDATION



DIMENSIONS ARE IN MILLIMETERS





DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX244
Low Voltage Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX244 contains eight non-inverting buffers with 3-STATE outputs. The device may be employed as a memory address driver, clock driver and bus-oriented transmitter/receiver. The LCX244 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 200V

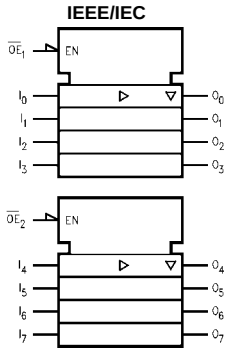
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

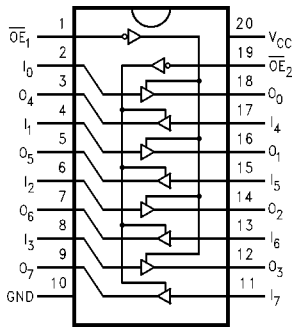
Order Number	Package Number	Package Description
74LCX244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 4.4mm Wide
74LCX244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V–3.6V		±24	mA
		V_{CC} = 2.7V–3.0V		±12	
		V_{CC} = 2.3V–2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC}	$T_A = -40°C$ to $+85°C$		Units
			(V)	Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}	Data to Output	1.5	6.5	1.5	7.5	1.5	7.8	
t_{PZL}	Output Enable Time	1.5	8.0	1.5	9.0	1.5	10.0	ns
t_{PZH}		1.5	8.0	1.5	9.0	1.5	10.0	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	8.0	1.5	8.4	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

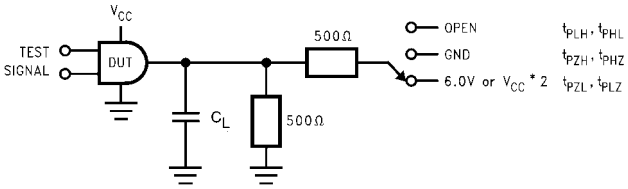
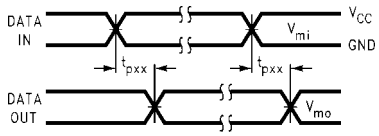
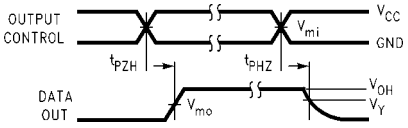


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

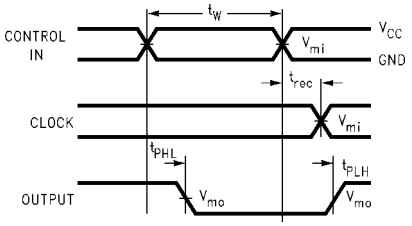
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



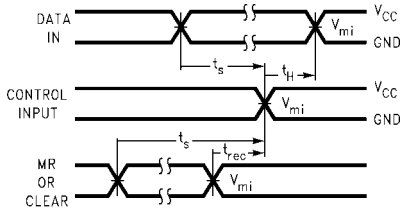
Waveform for Inverting and Non-Inverting Functions



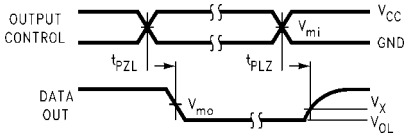
3-STATE Output High Enable and Disable Times for Logic



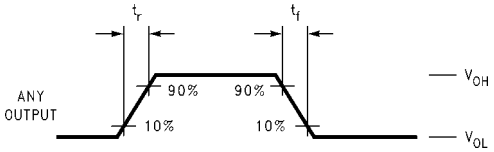
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic



t_{rise} and t_{fall}

FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

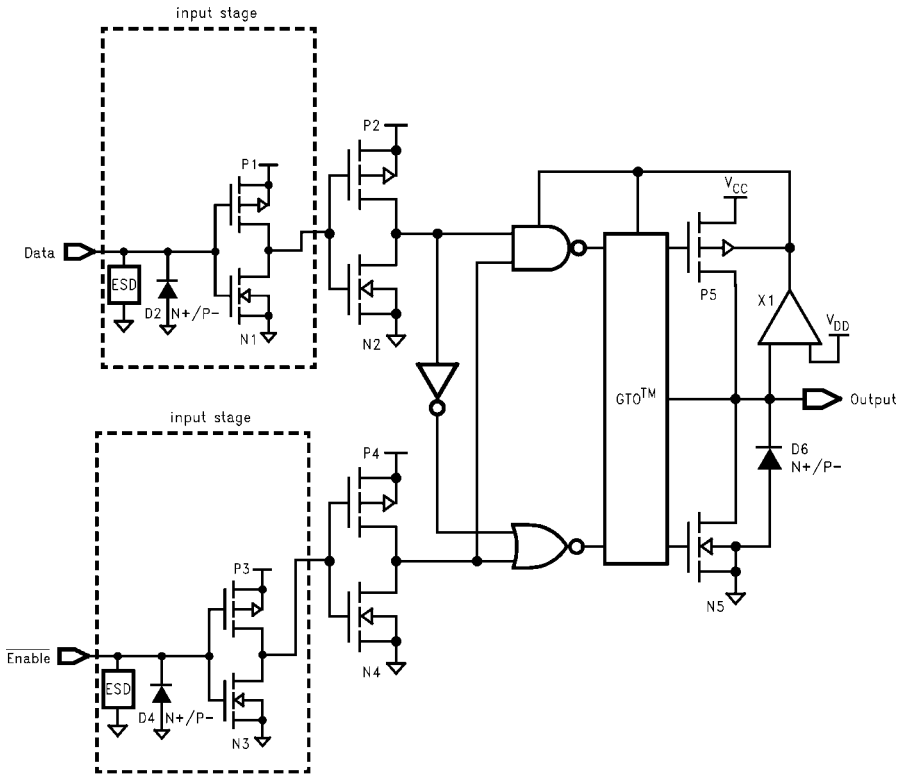
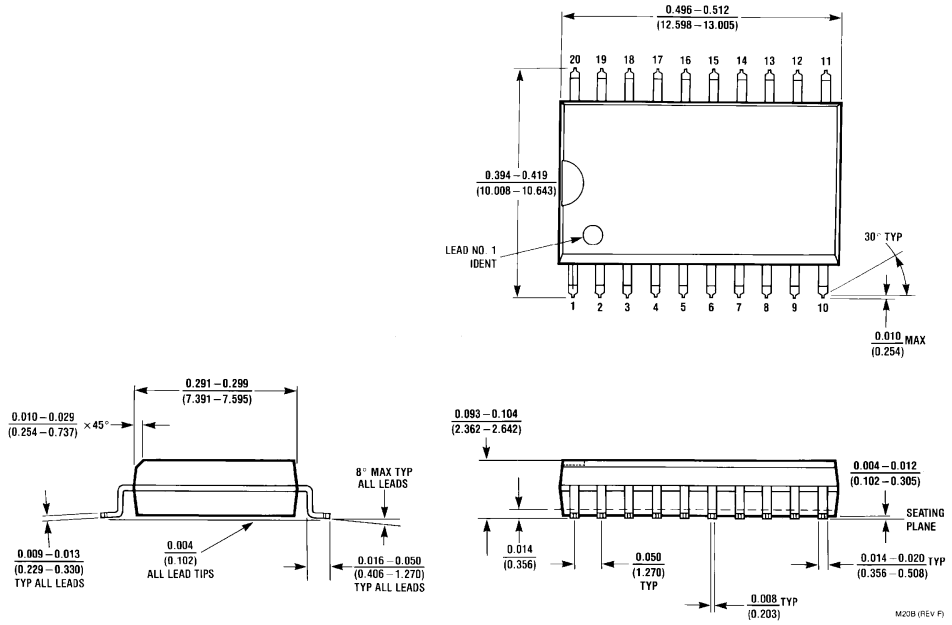
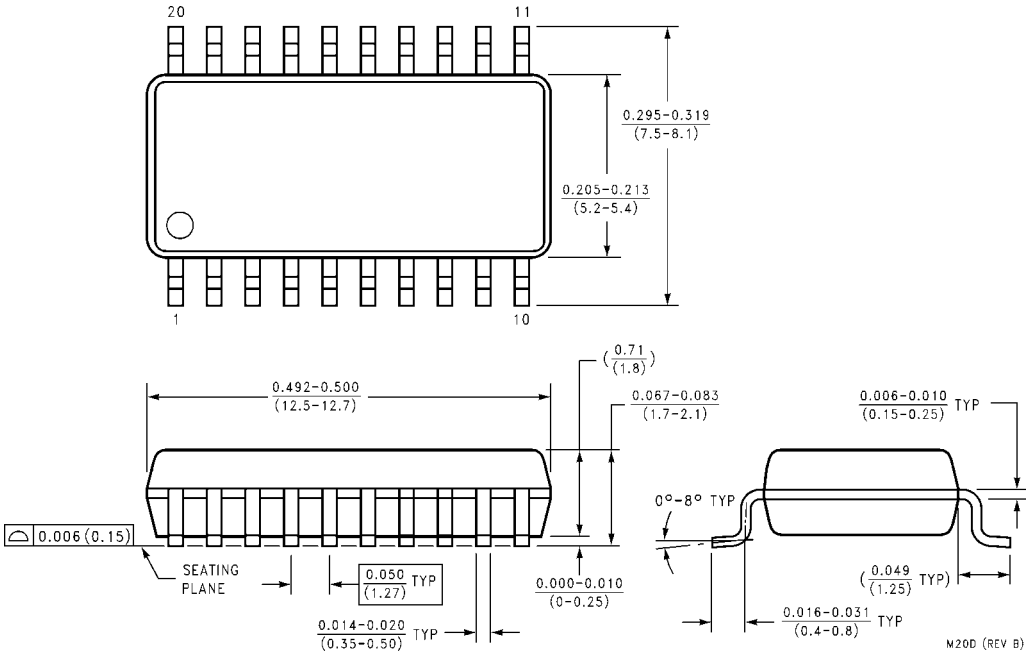


FIGURE 3.

Physical Dimensions inches (millimeters) unless otherwise noted

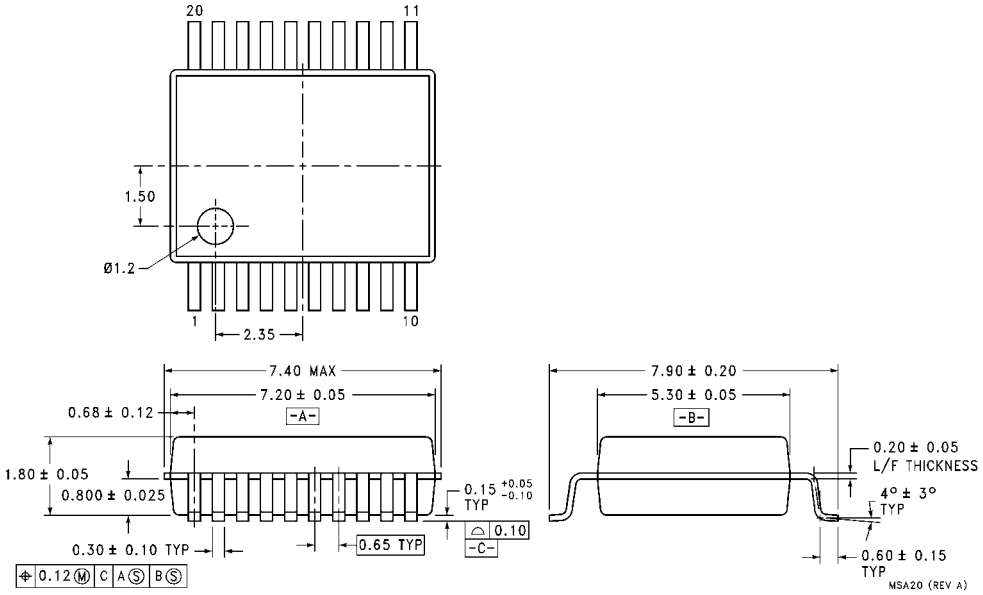


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



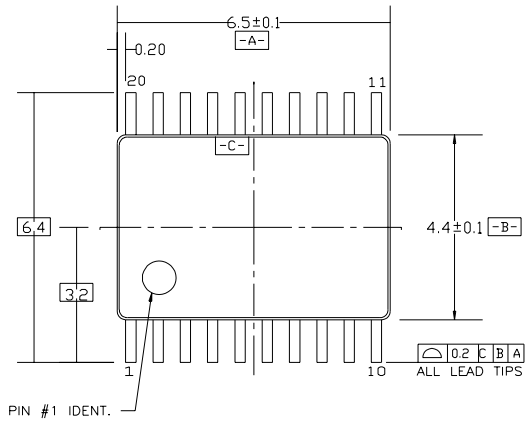
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 4.4mm Wide
Package Number M20D

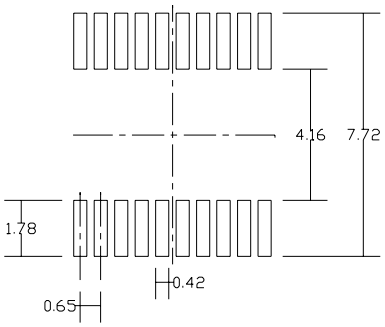
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



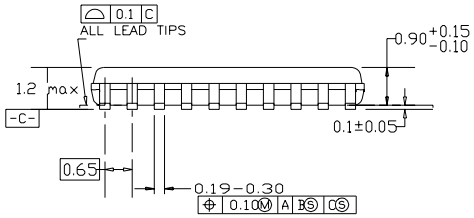
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

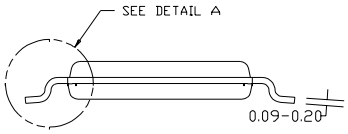
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

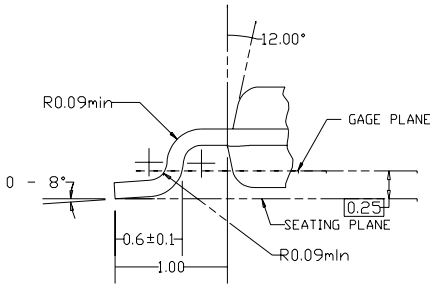




LAND PATTERN RECOMMENDATION







DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised May 1999

74LCX245

Low Voltage Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V and 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The T/$\overline{R}$ input determines the direction of data flow through the device. The $\overline{OE}$ input disables both the A and B ports by placing them in a high impedance state.

The LCX245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 200V

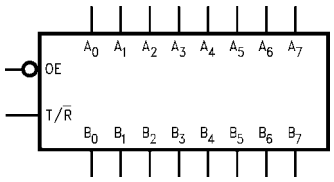
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

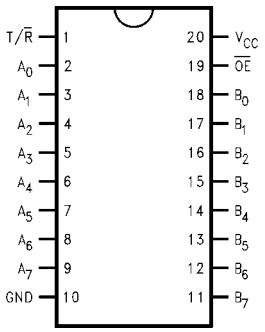
Order Number	Package Number	Package Description
74LCX245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ Type II, 4.4mm Wide
74LCX245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ Type II, 5.3mm Wide
74LCX245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

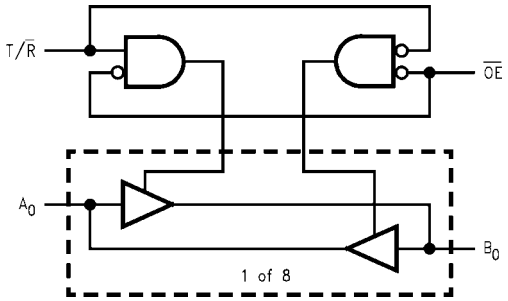
Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus $B_0 – B_7$ Data to Bus $A_0 – A_7$
L	H	Bus $A_0 – A_7$ Data to Bus $B_0 – B_7$
H	X	HIGH Z State on $A_0 – A_7$, $B_0 – B_7$ (Note 2)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Note 2: Unused bus terminals during HIGH Z State must be held HIGH or LOW.

Logic Diagram



Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 4)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V - 3.0V		±12	
		V_{CC} = 2.3V - 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 - 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 - 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V	2.3 − 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 6)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 7)		1.0					

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

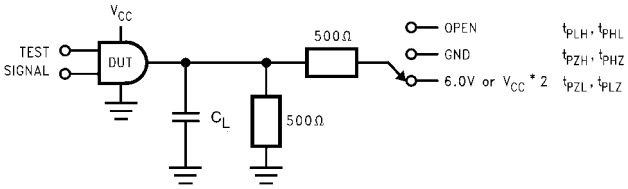
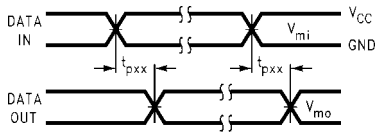
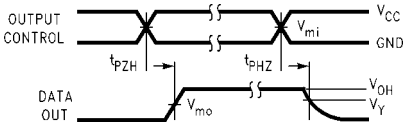


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

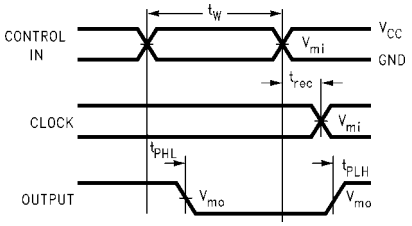
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



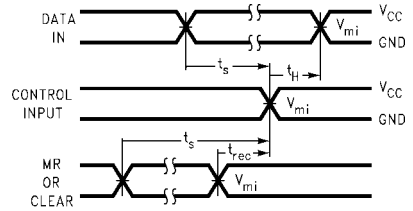
Waveform for Inverting and Non-Inverting Functions



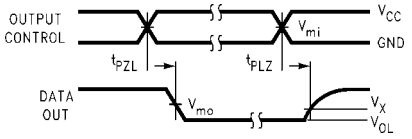
3-STATE Output High Enable and Disable Times for Logic



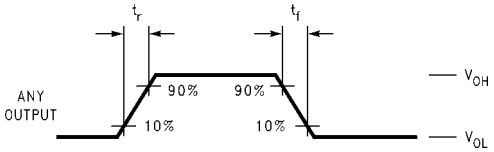
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

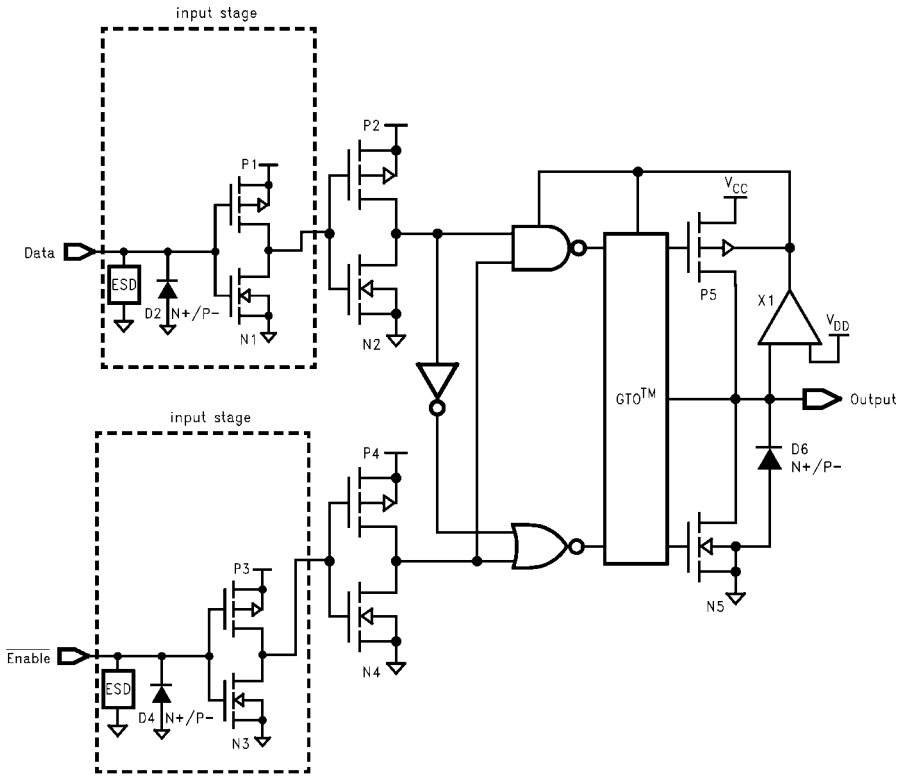


t_{rise} and t_{fall}

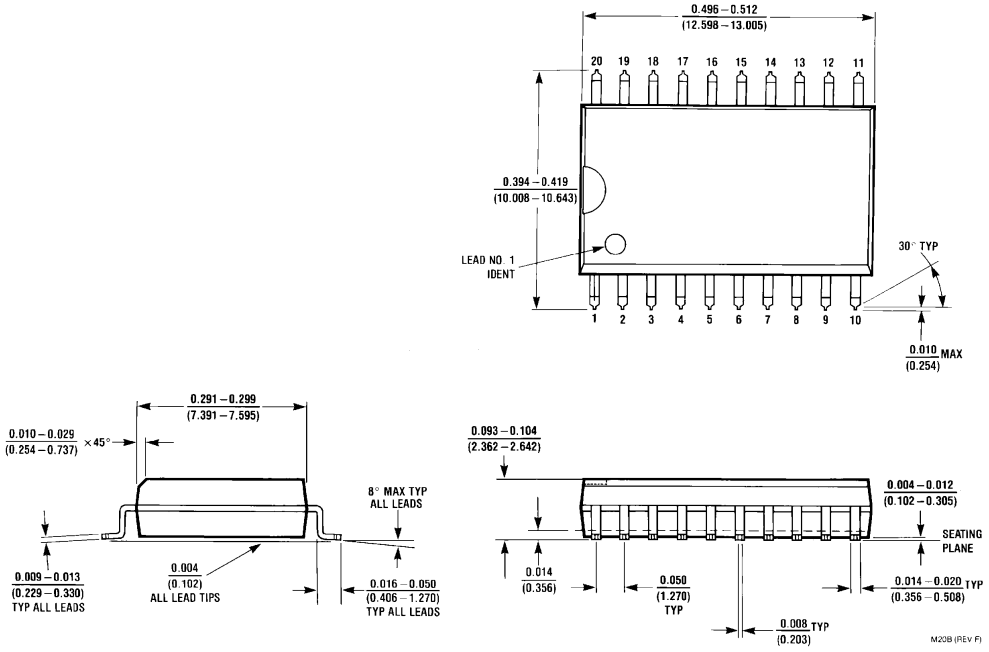
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

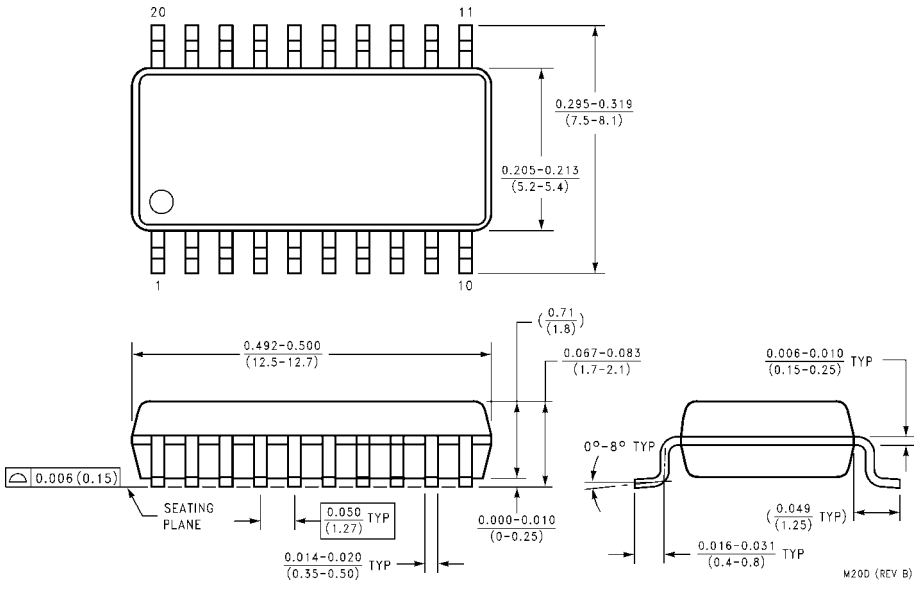
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

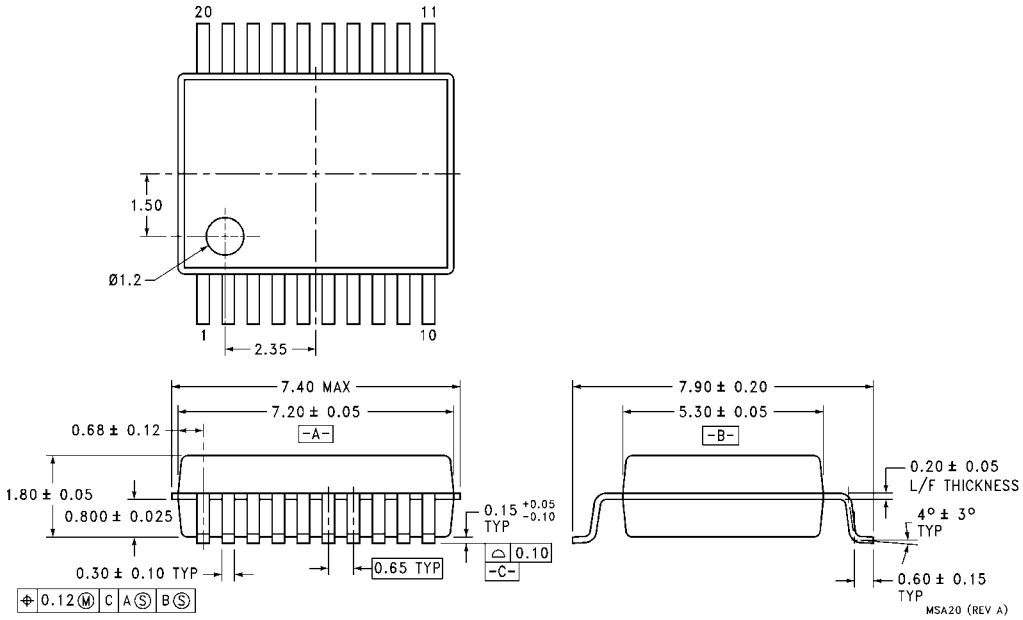


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



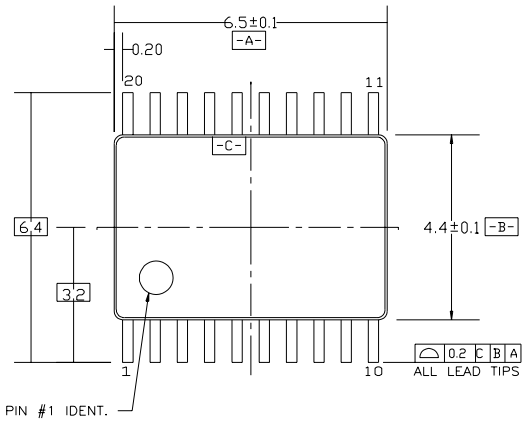
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 4.4mm Wide
Package Number M20D

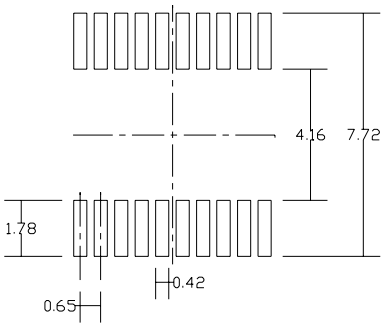
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



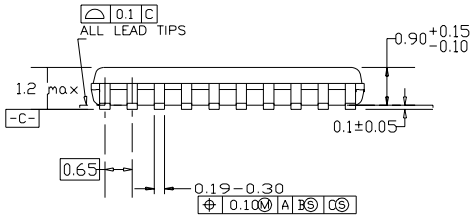
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

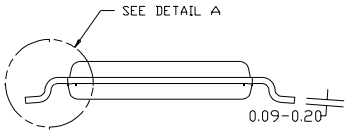
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

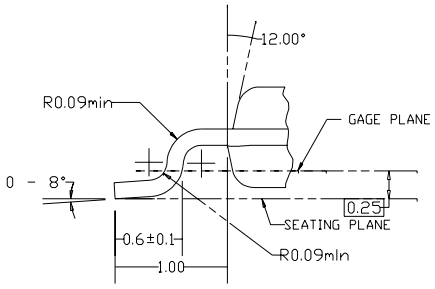




LAND PATTERN RECOMMENDATION







DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1995
Revised April 1999

74LCX257
Low Voltage Quad 2-Input Multiplexer with 5V Tolerant Inputs and Outputs

General Description

The LCX257 is a quad 2-input multiplexer with 3-STATE outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (non inverted) form. The outputs may be switched to a high impedance state by placing a logic HIGH on the common Output Enable ($\overline{OE}$) input, allowing the outputs to interface directly with bus-oriented systems.

The 74LCX257 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

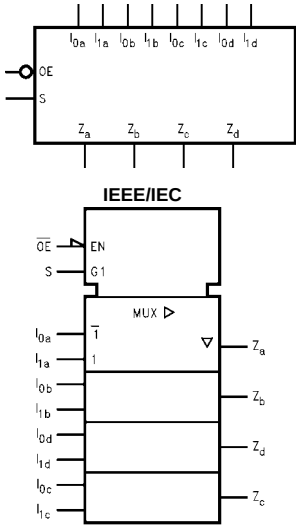
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

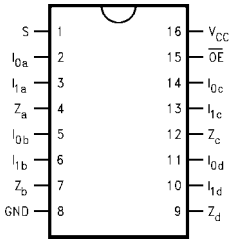
Order Number	Package Number	Package Description
74LCX257M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow
74LCX257SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX257MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
S	Common Data Select Input
$\overline{OE}$	3-STATE Output Enable Input
I_{0a}–I_{0d}	Data Inputs from Source 0
I_{1a}–I_{1d}	Data Inputs from Source 1
Z_a–Z_d	3-STATE Multiplexer Outputs

Functional Description

The LCX257 is a quad 2-input multiplexer with 3-STATE outputs. It selects four bits of data from two sources under control of a Common Data Select input. When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The data on the selected inputs appears at the outputs in true (non inverted) form. The device is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$Z_a = \overline{OE} \bullet (1_{1a} \bullet S + I_{0a} \bullet \overline{S})$

$Z_b = \overline{OE} \bullet (1_{1b} \bullet S + I_{0b} \bullet \overline{S})$

$Z_c = \overline{OE} \bullet (1_{1c} \bullet S + I_{0c} \bullet \overline{S})$

$Z_d = \overline{OE} \bullet (1_{1d} \bullet S + I_{0d} \bullet \overline{S})$

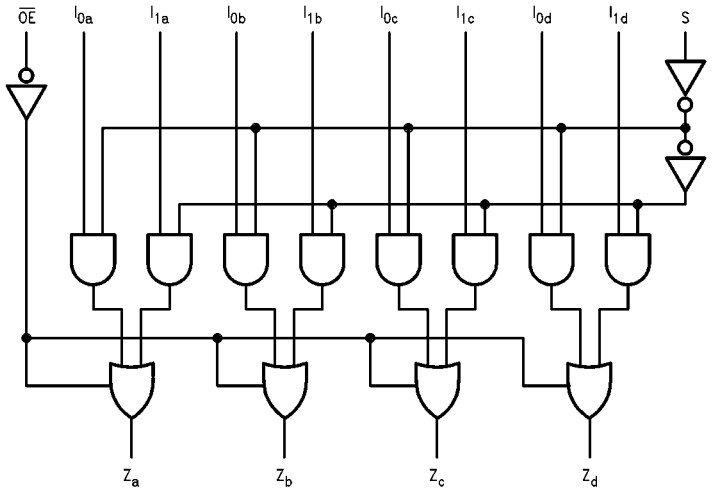
When the Output Enable ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure the Output Enable signals to 3-STATE devices whose outputs are tied together are designed so there is no overlap.

Truth Table

Output Enable	Select Input	Data Inputs		Outputs
$\overline{OE}$	S	I_0	I_1	Z
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum rating must be observed.

Note 4: Unused Inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.5	1.5	9.1	ns
t_{PLH}	S→Zn	1.5	7.0	1.5	8.5	1.5	9.1	
t_{PHL}	Propagation Delay	1.5	6.0	1.5	6.5	1.5	7.2	ns
t_{PLH}	In→Zn	1.5	6.0	1.5	6.5	1.5	7.2	
t_{PZL}	Output Enable Time	1.5	7.0	1.5	8.5	1.5	9.1	ns
t_{PZH}	OE →Zn	1.5	7.0	1.5	8.5	1.5	9.1	
t_{PLZ}	Output Disable Time	1.5	5.5	1.5	6.0	4.0	6.6	ns
t_{PHZ}	OE →Zn	1.5	5.5	1.5	6.0	2.0	6.6	
t_{OSHL}	Output to Output Skew (Note 6)		1.0			4.0		ns
t_{OSLH}			1.0			4.0		

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

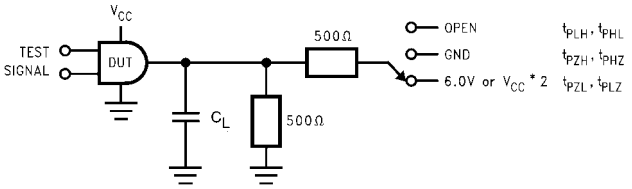
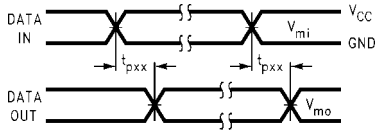
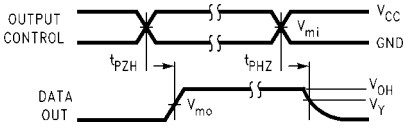


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

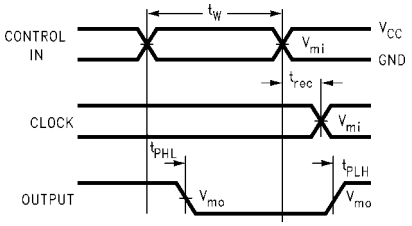
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



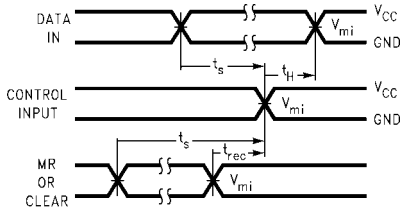
Waveform for Inverting and Non-Inverting Functions



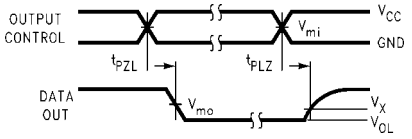
3-STATE Output High Enable and Disable Times for Logic



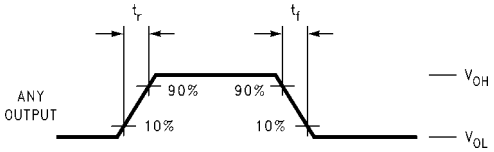
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

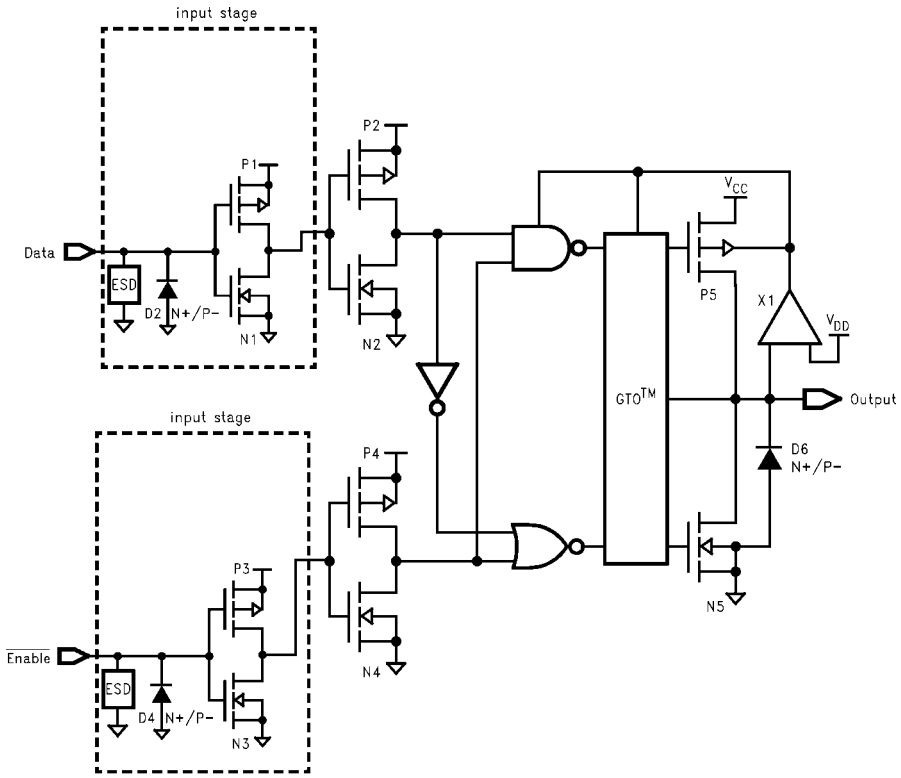


t_{rise} and t_{fall}

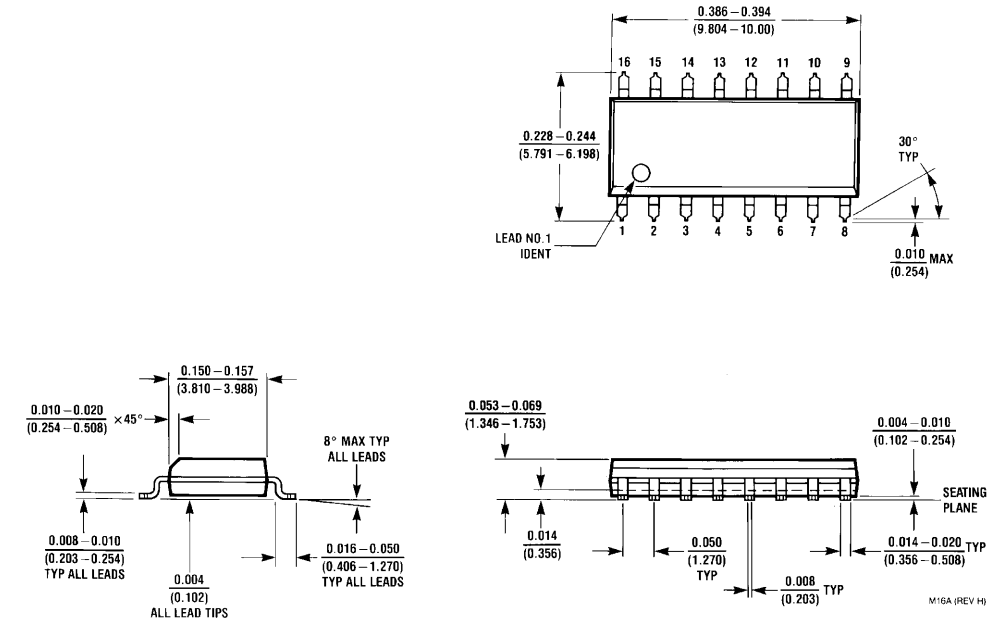
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

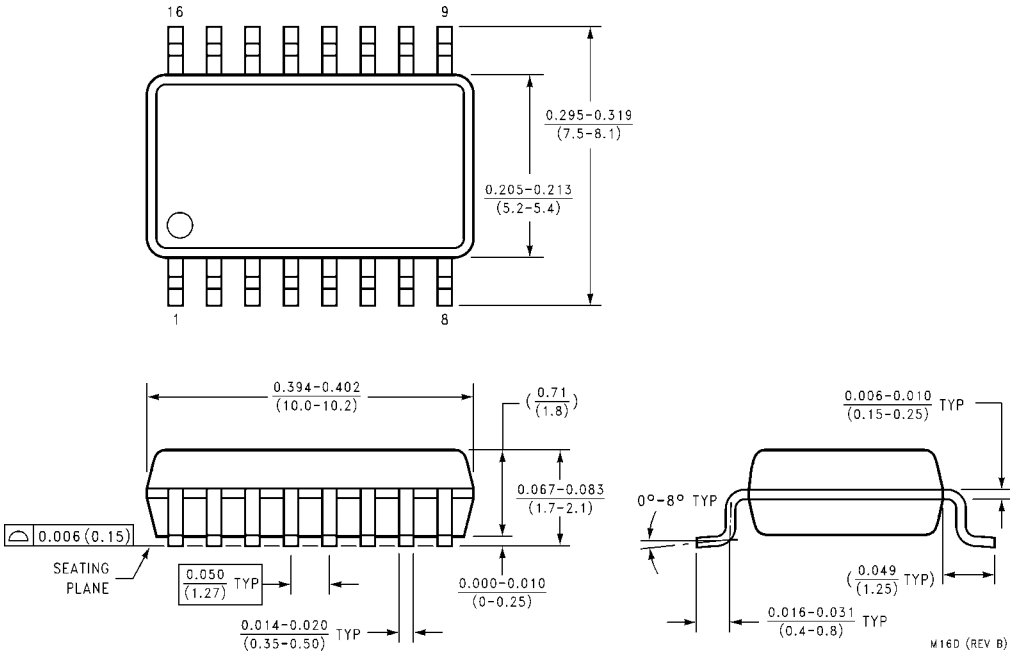
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

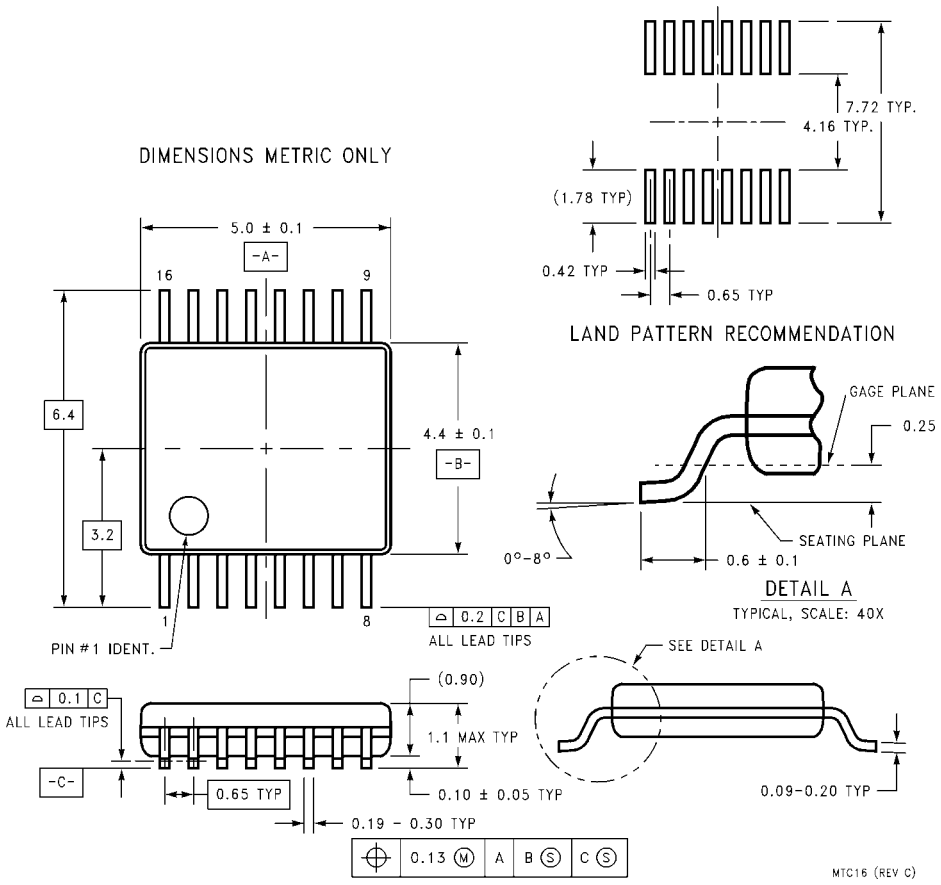


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised March 1999

74LCX32
Low Voltage Quad 2-Input OR Gate with 5V Tolerant Inputs

General Description

The LCX32 contains four 2-input OR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX32 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

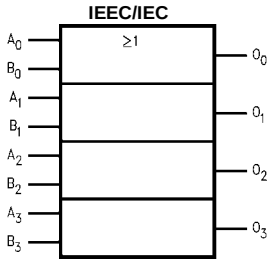
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 150V

Ordering Code:

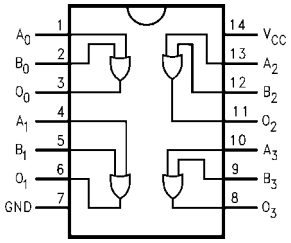
Order Number	Package Number	Package Description
74LCX32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = –40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.2	1.5	6.6	ns
t_{PLH}		1.5	5.5	1.5	6.2	1.5	6.6	
t_{OSHL}	Output to Output		1.0					ns
t_{OSLH}	Skew (Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

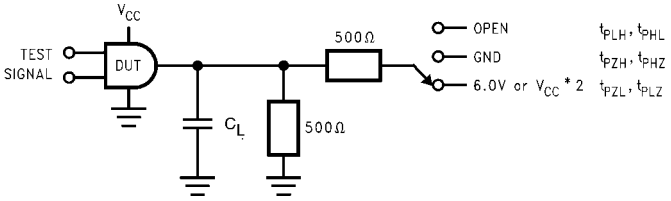
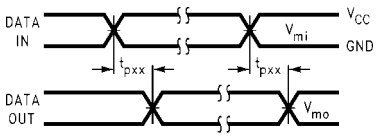
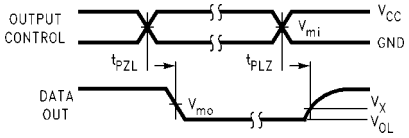


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

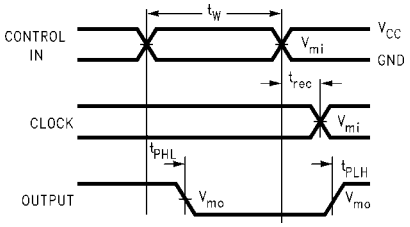
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



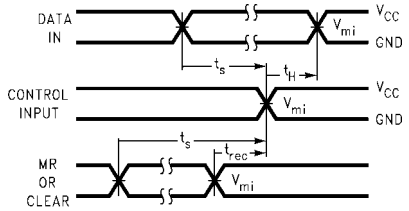
Waveform for Inverting and Non-Inverting Functions



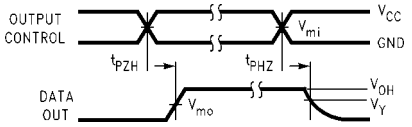
3-STATE Output Low Enable and DIsable Times for Logic



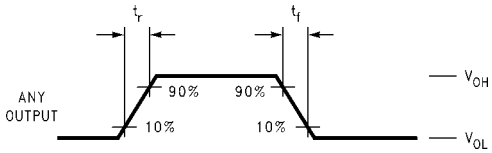
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

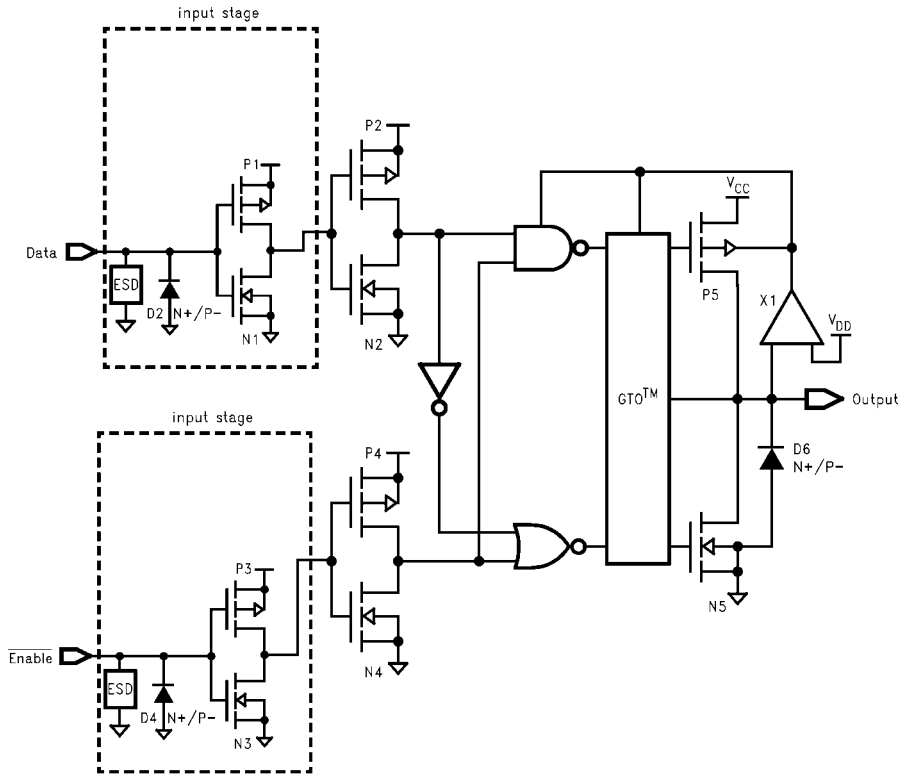


t_{rise} and t_{fall}

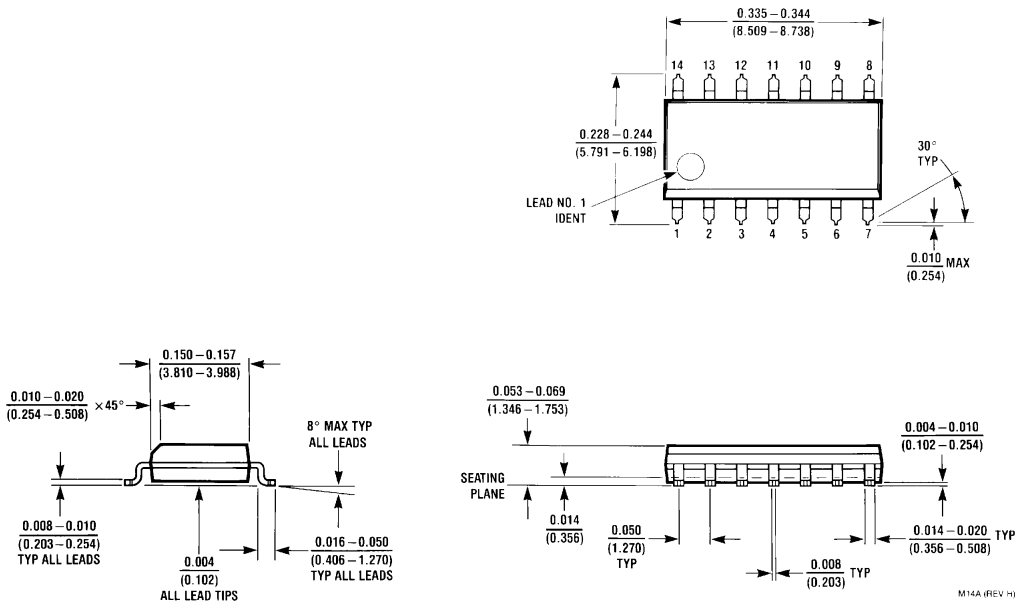
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

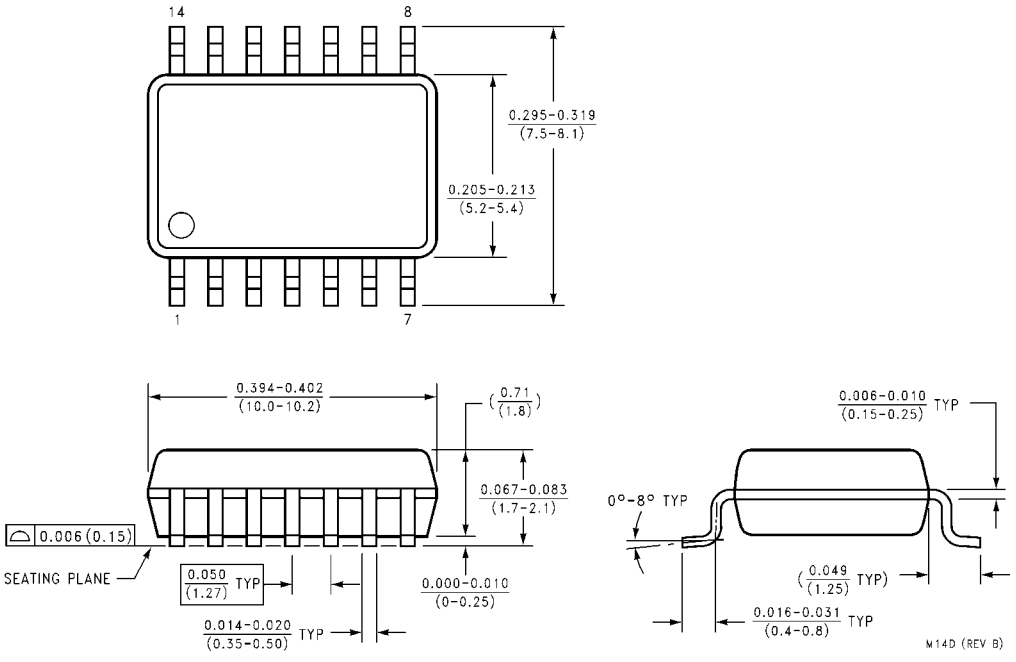
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

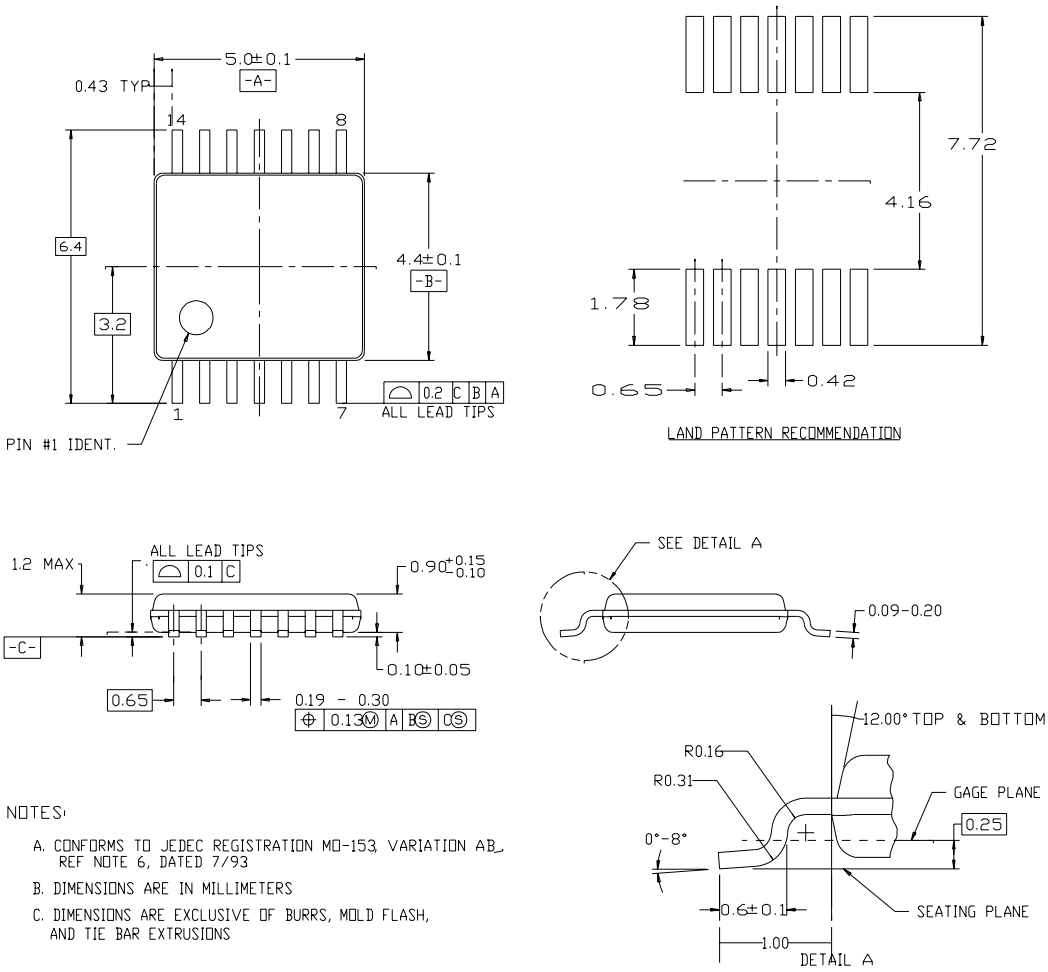


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX373

Low Voltage Octal Transparent Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX373 consists of eight latches with 3-STATE outputs for bus organized system applications. The device is designed for low voltage (3.3V or 2.5V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 8.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human Body Model > 2000V
  - Machine Model > 200V

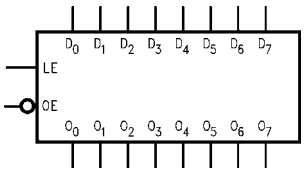
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

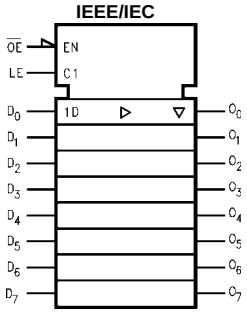
Order Number	Package Number	Package Description
74LCX373WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX373MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

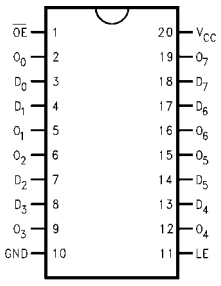
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Truth Table

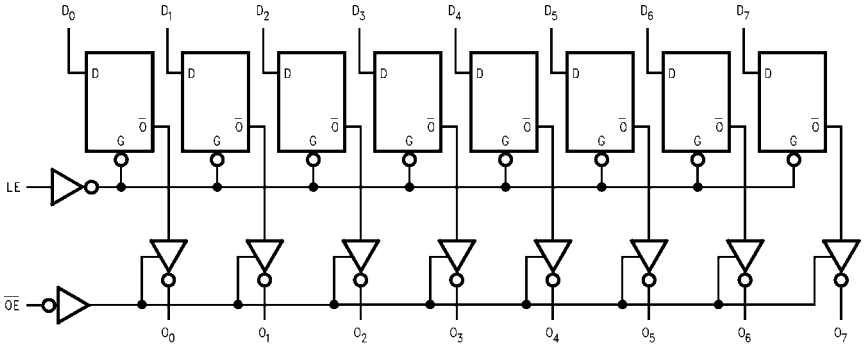
Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Functional Description

The LCX373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50pF$		$C_L = 50pF$		$C_L = 30pF$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	8.0	1.5	9.0	1.5	9.6	ns
t_{PLH}	D_n to O_n	1.5	8.0	1.5	9.0	1.5	9.6	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	LE to O_n	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	
t_S	Setup Time, D_n to LE	2.5		2.5		4.0		ns
t_H	Hold Time, D_n to LE	1.5		1.5		2.0		ns
t_W	LE Pulse Width	3.3		3.3		4.0		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 6)		1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$pF, $V_I = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$pF, $V_I = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

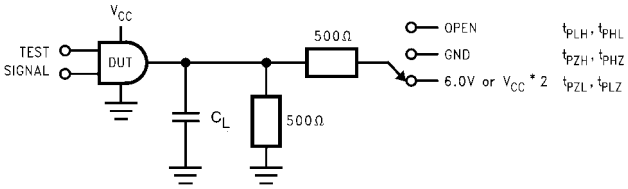
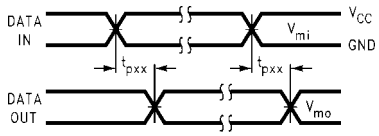
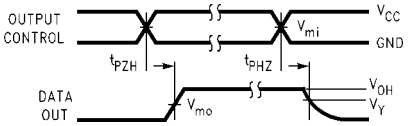


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

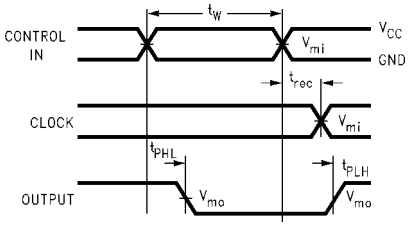
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



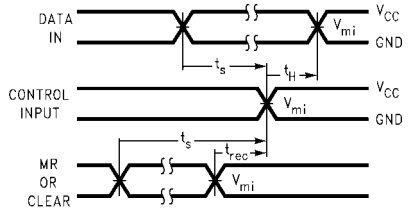
Waveform for Inverting and Non-Inverting Functions



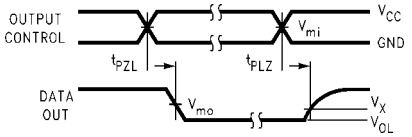
3-STATE Output High Enable and Disable Times for Logic



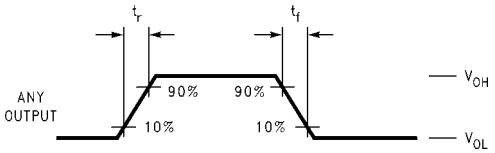
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

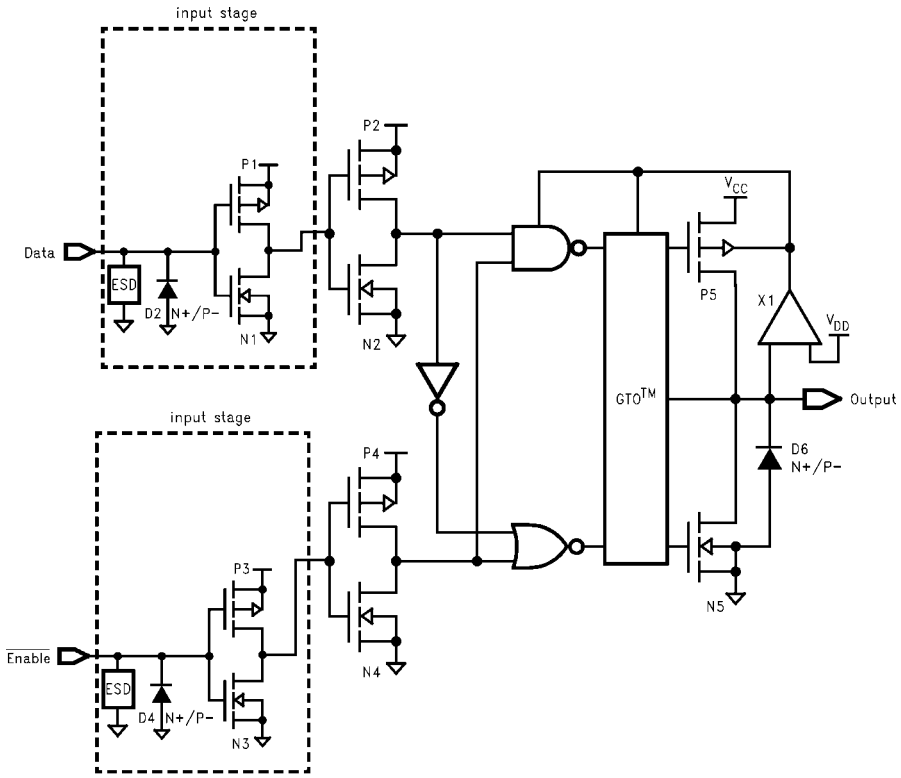


t_{rise} and t_{fall}

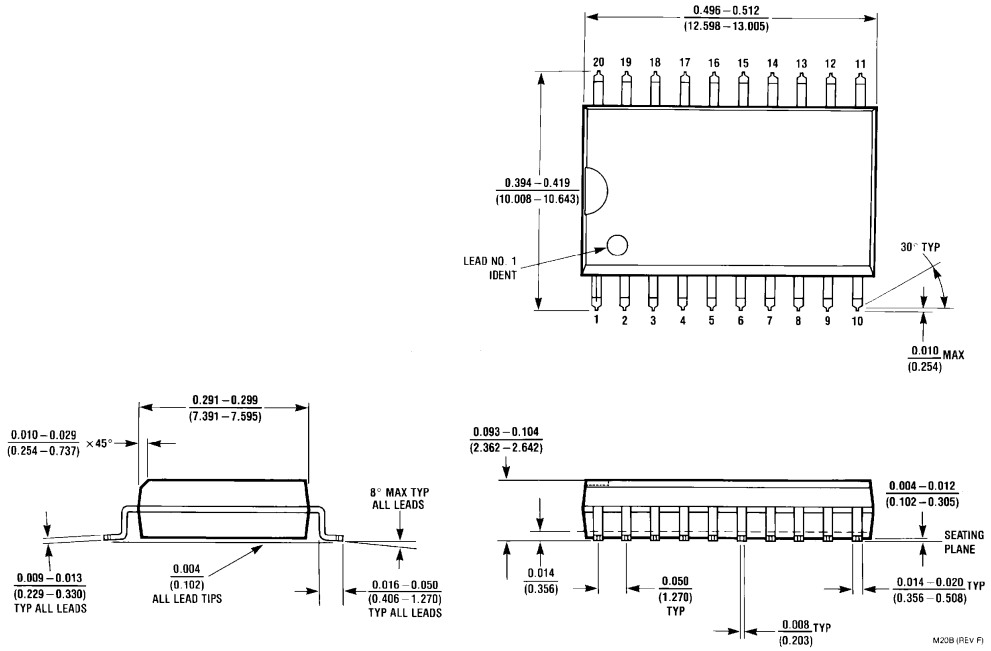
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

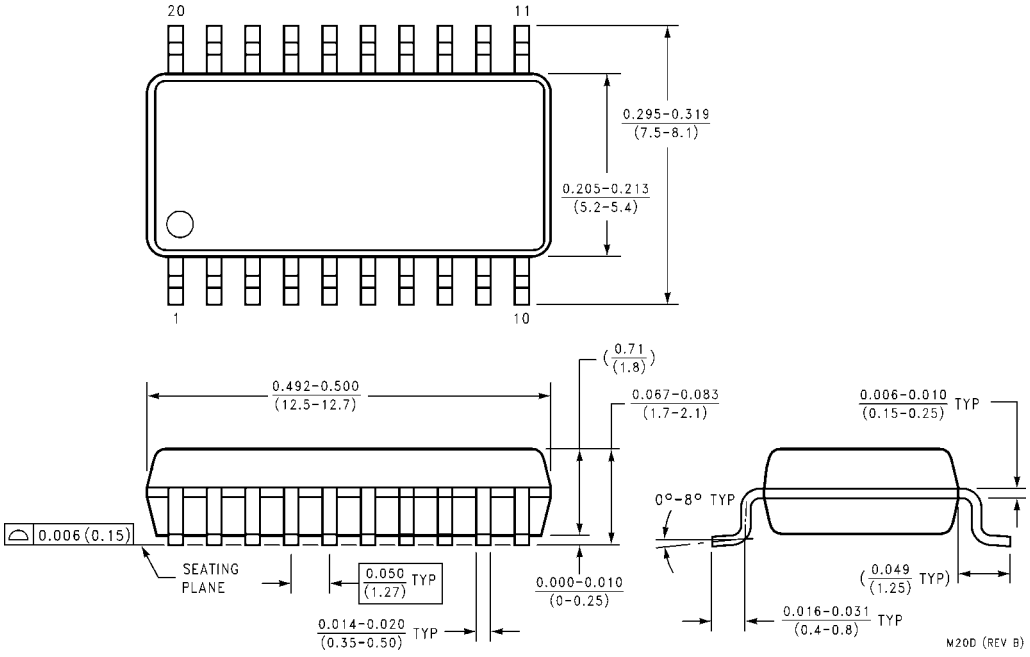
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

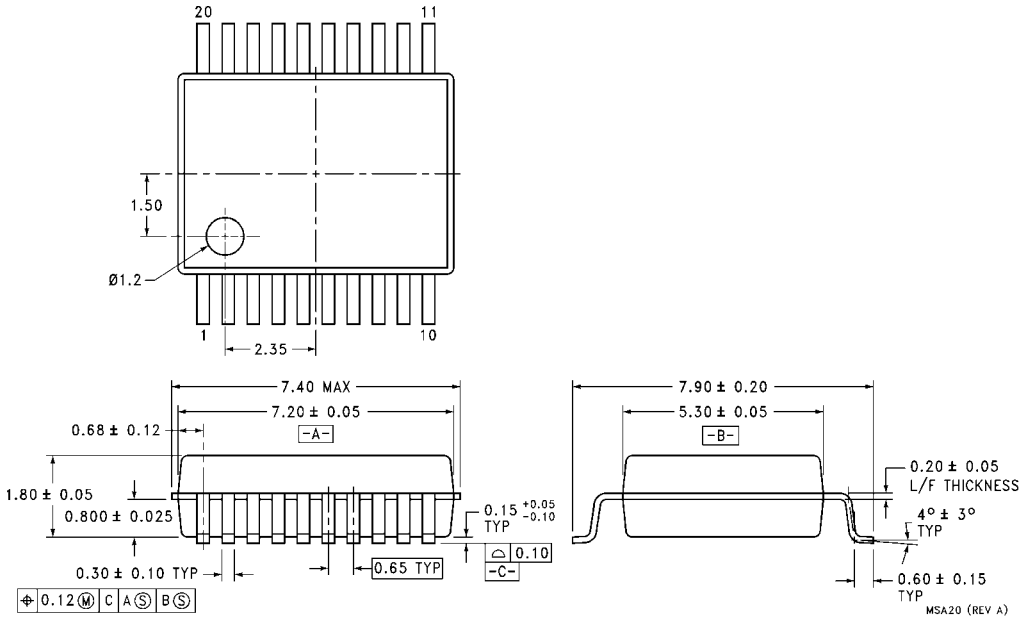


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



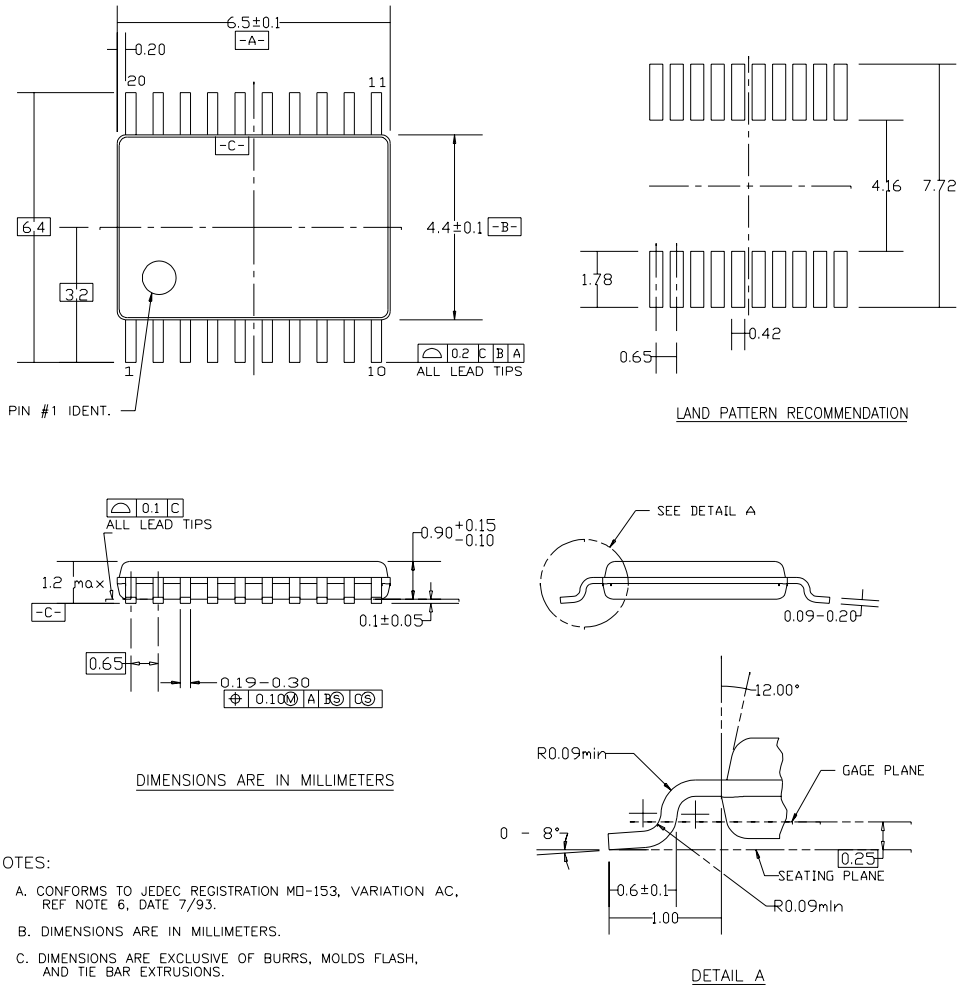
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX374

Low Voltage Octal D-Type Flip-Flop with 5V Tolerant Inputs and Outputs

General Description

The LCX374 consists of eight D-type flip-flops featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops. The LCX374 is designed for low-voltage (3.3V or 2.5V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 8.5 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human Body Model > 2000V
  Machine Model > 200V

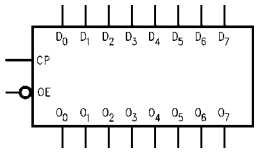
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

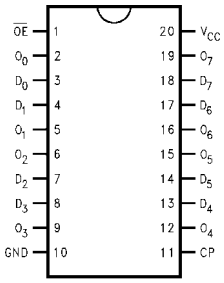
Order Number	Package Number	Package Description
74LCX374WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX374MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

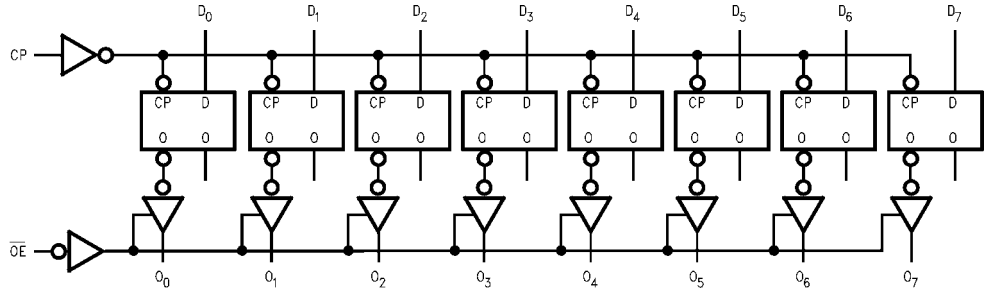
The LCX374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	L	L	O_0
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
O_0 = Previous O_0 before HIGH-to-LOW of CP

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5 \pm 0.2$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150		150		150		MHz
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	CP to O_n	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	
t_S	Setup Time	2.5		2.5		4.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.3		3.3		4.0		ns
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

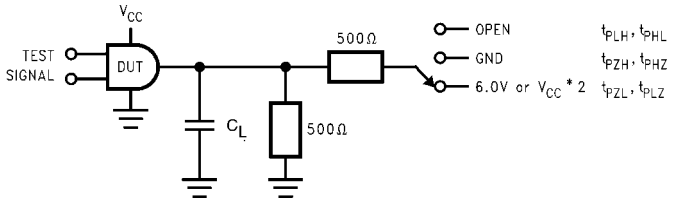
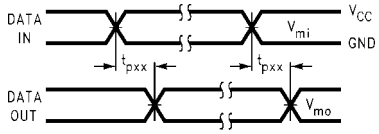
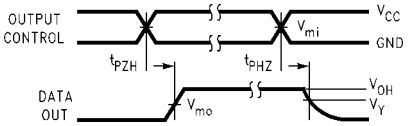


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

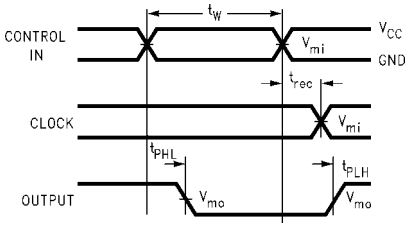
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



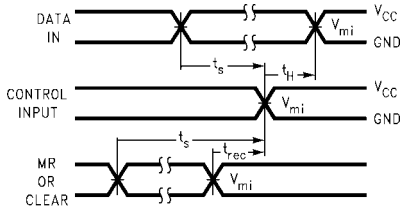
Waveform for Inverting and Non-Inverting Functions



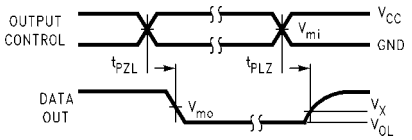
3-STATE Output High Enable and Disable Times for Logic



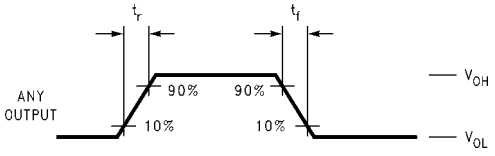
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

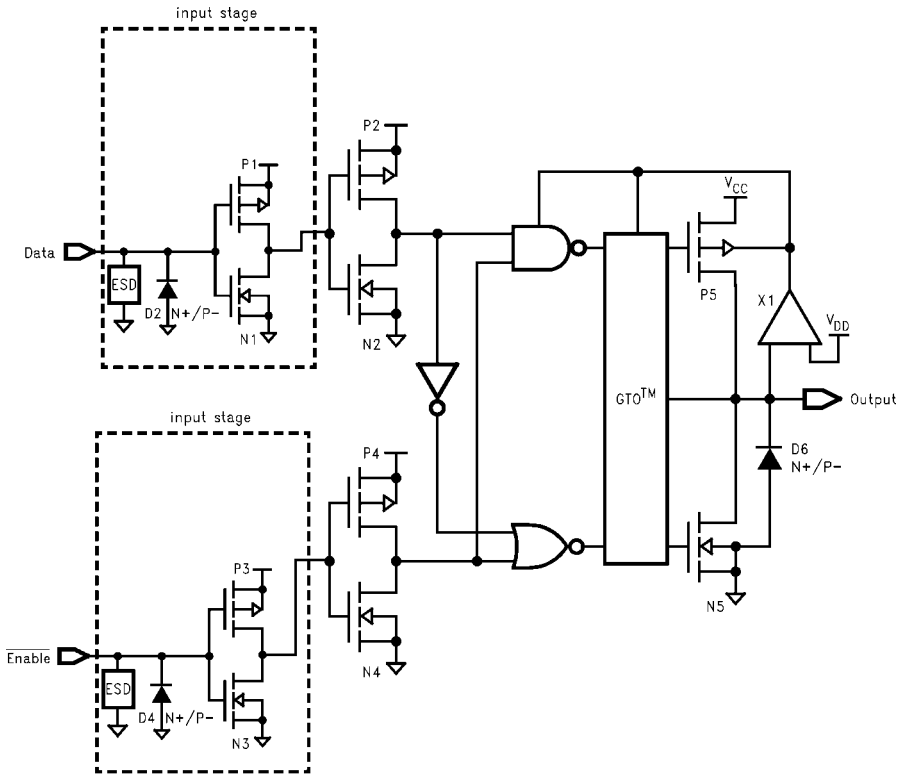


t_{rise} and t_{fall}

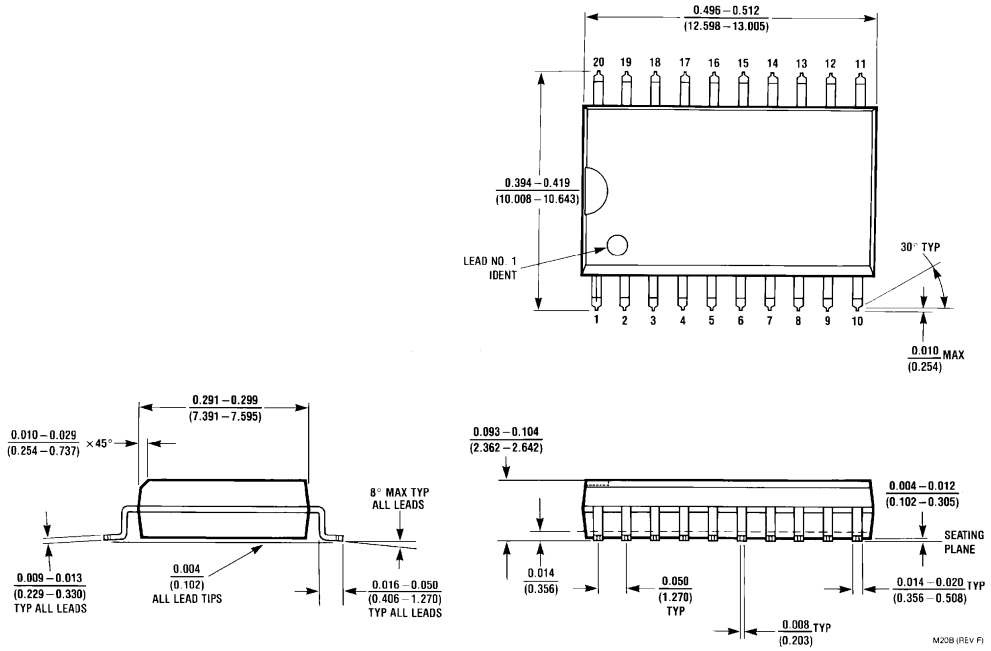
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

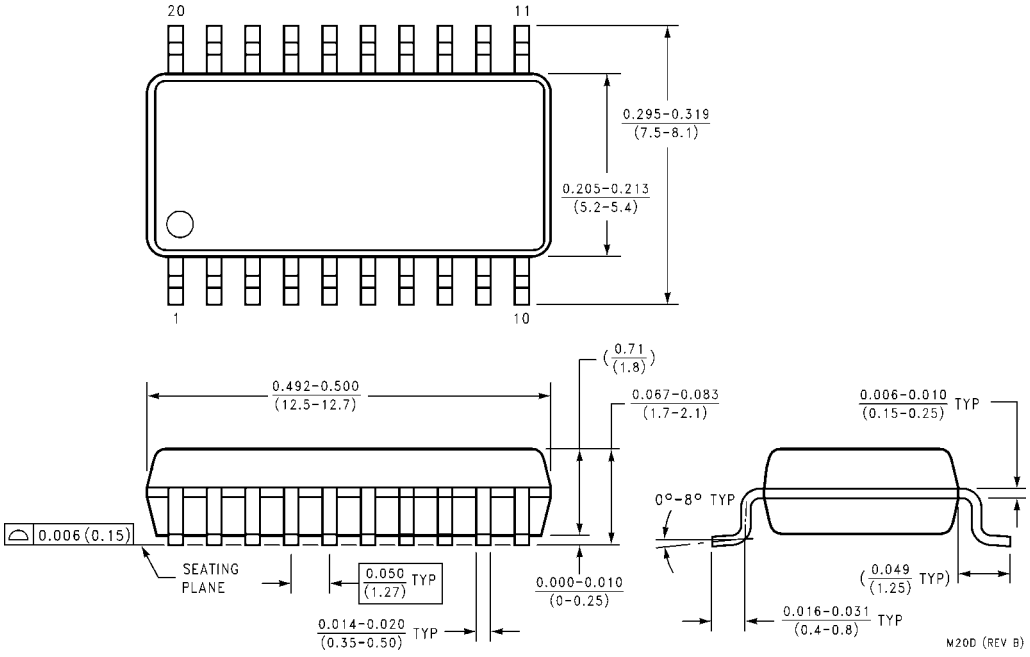
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

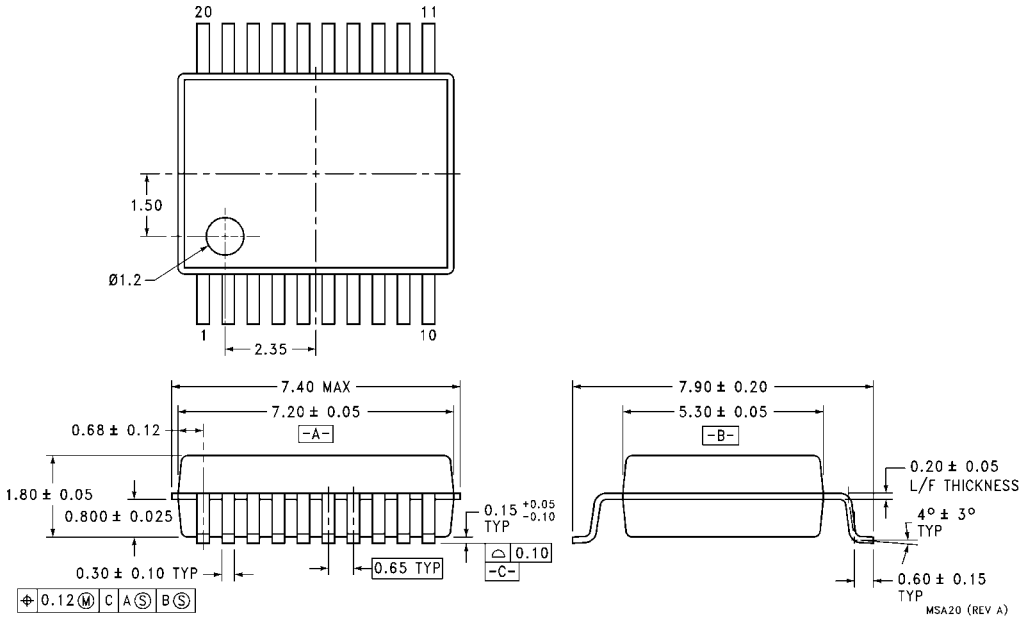


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



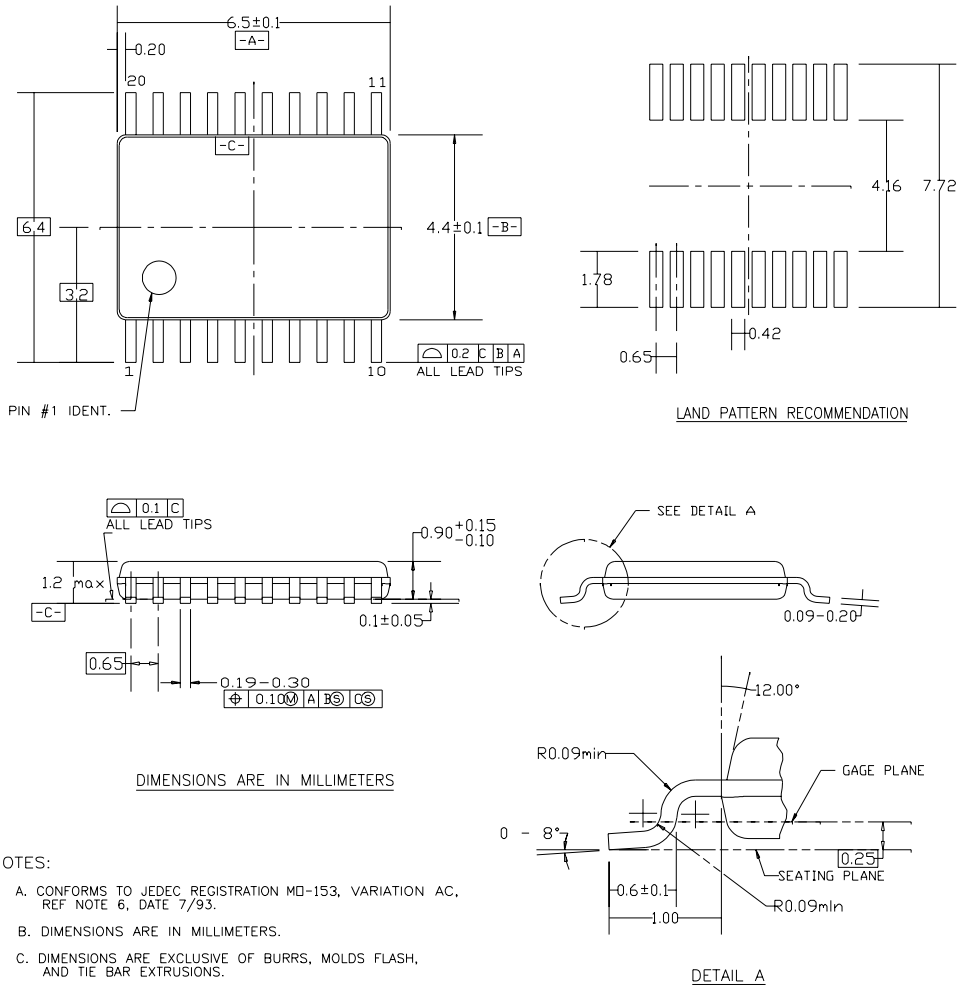
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ, TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mmWide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1995
Revised June 1999

74LCX38
Low Voltage Quad 2-Input NAND Gate (Open Drain) with 5V Tolerant Inputs

General Description

The LCX38 contains four 2-input open drain NAND gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX38 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

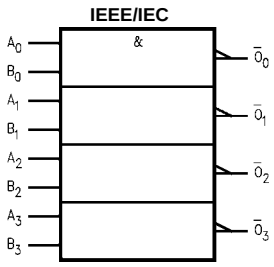
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 150V

Ordering Code:

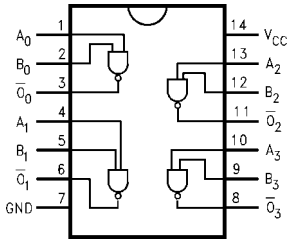
Order Number	Package Number	Package Description
74LCX38M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX38SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX38MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those beyond which the safety of the device cannot be guaranteed. The device should not be operating at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.3 – 3.6		0.8	
V_{OL}	LOW Level Output Voltage	I_{OL} = 100μA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	μA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	μA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.3 – 3.6		500	μA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PZL}	Propagation Delay Time	1.5	5.0	1.5	5.5	1.5	6.5	ns
t_{PLZ}		1.5	5.0	1.5	5.5	1.5	6.0	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

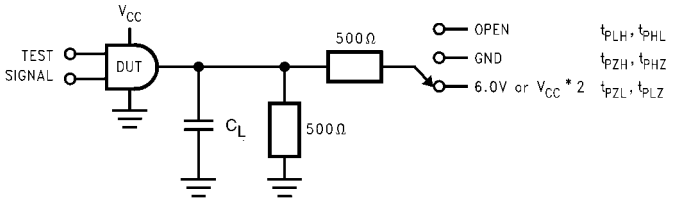
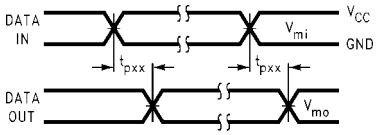
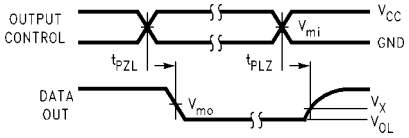


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

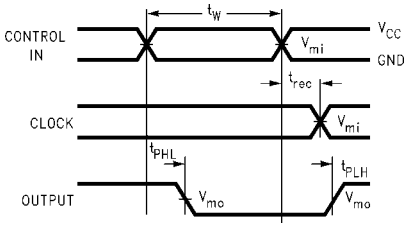
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



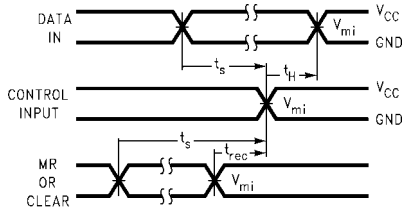
Waveform for Inverting and Non-Inverting Functions



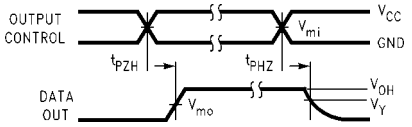
3-STATE Output Low Enable and Disable Times for Logic



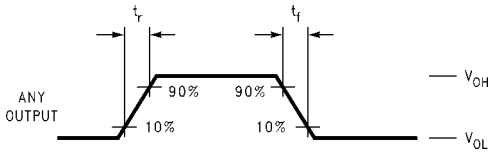
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

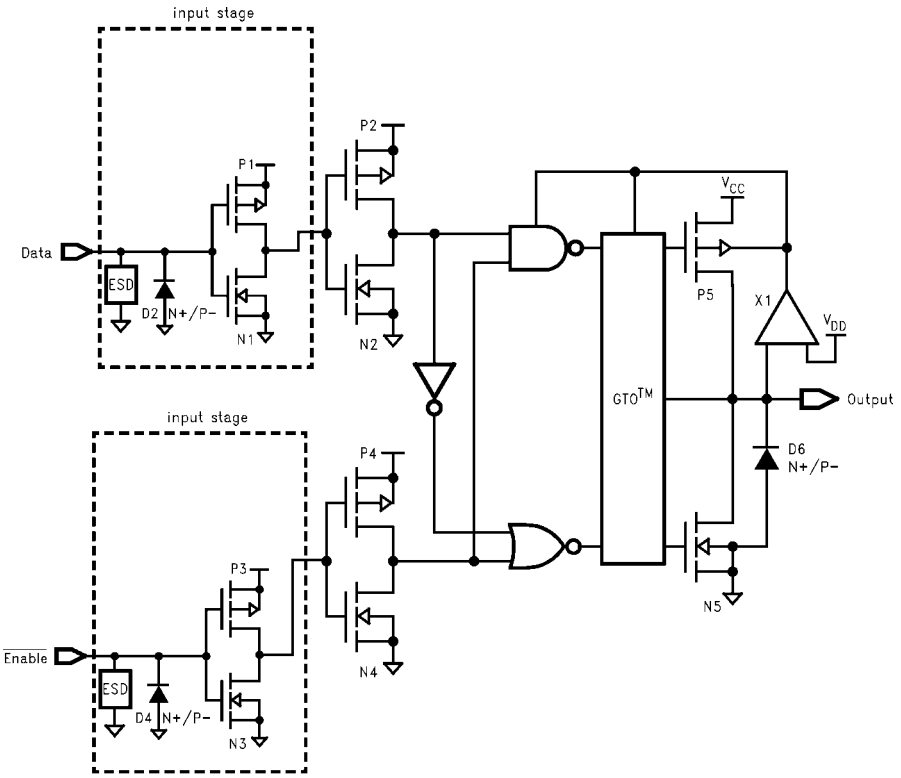


t_{rise} and t_{fall}

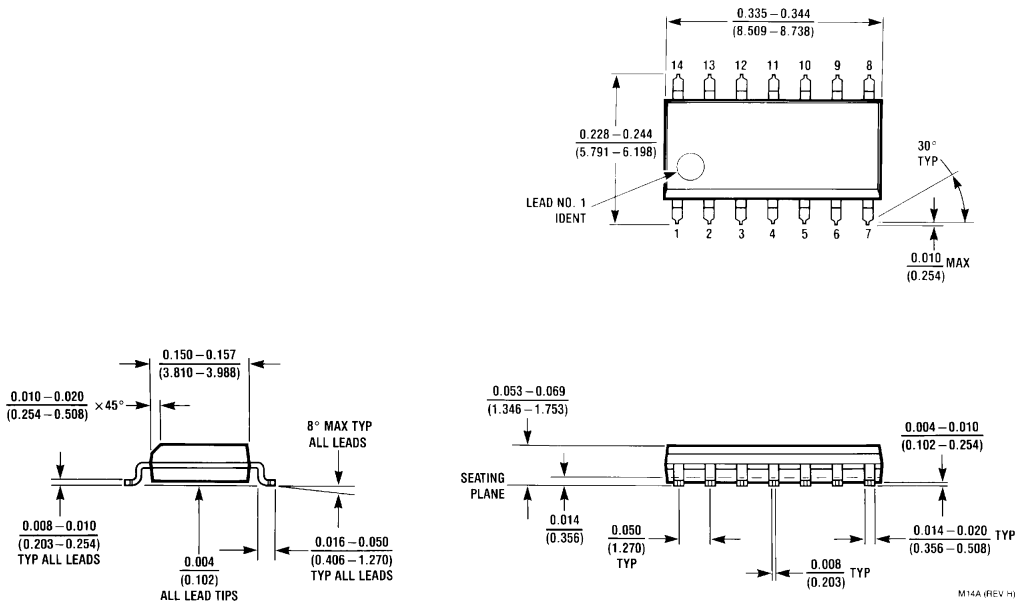
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

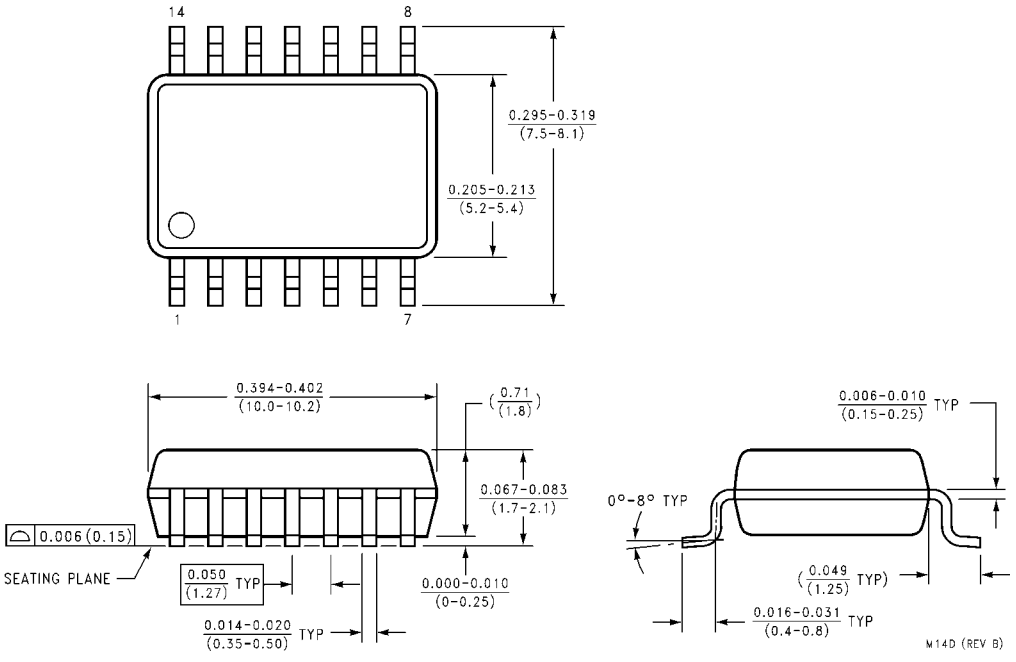
Schematic Diagram



Physical Dimensions inches (millimeters) unless otherwise noted

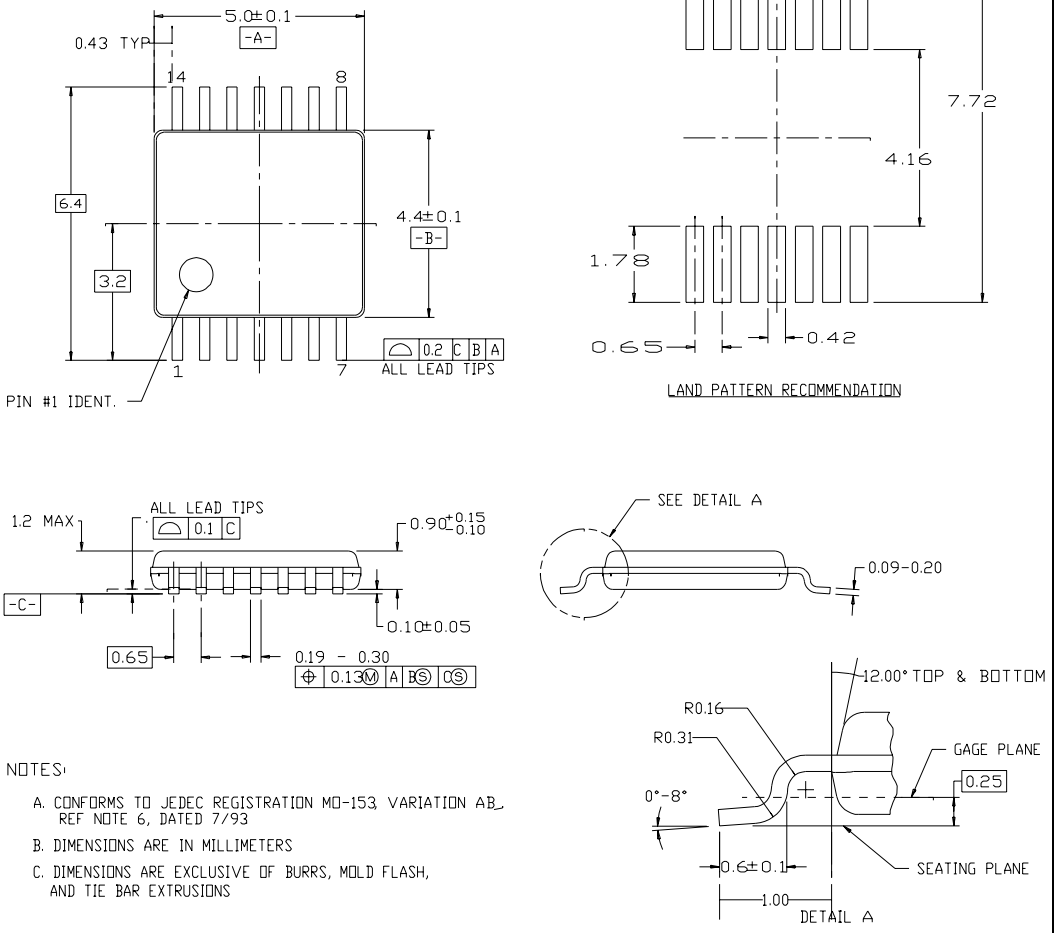


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX540

Low Voltage Octal Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX540 is an octal buffer/line driver designed to be employed as a memory and address driver, clock driver and bus oriented transmitter/receiver.

This device is similar in function to the LCX240 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

The LCX540 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The LCX540 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

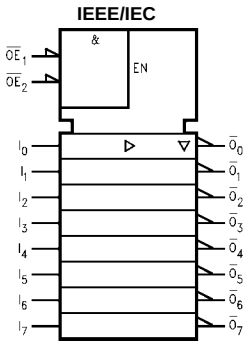
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

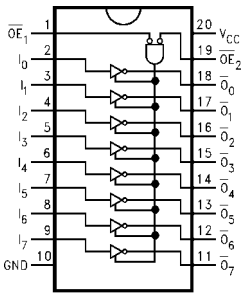
Order Number	Package Number	Package Description
74LCX540WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX540SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX540MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), TYPE II, 5.3mm Wide
74LCX540MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	$\overline{O}_n$
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50pF$		$C_L = 50pF$		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}		1.5	6.5	1.5	7.5	1.5	7.8	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	−0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

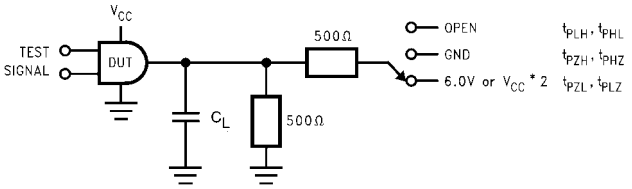
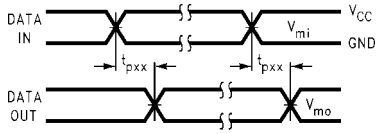
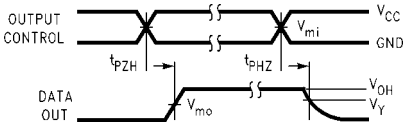


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

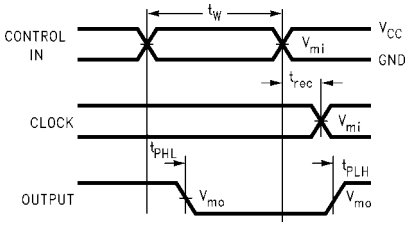
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



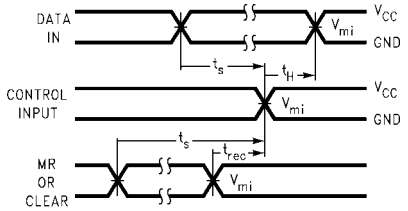
Waveform for Inverting and Non-Inverting Functions



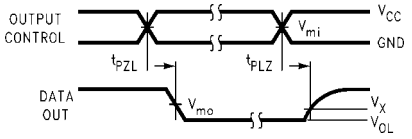
3-STATE Output High Enable and Disable Times for Logic



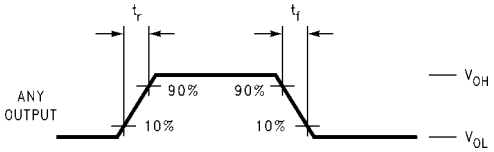
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

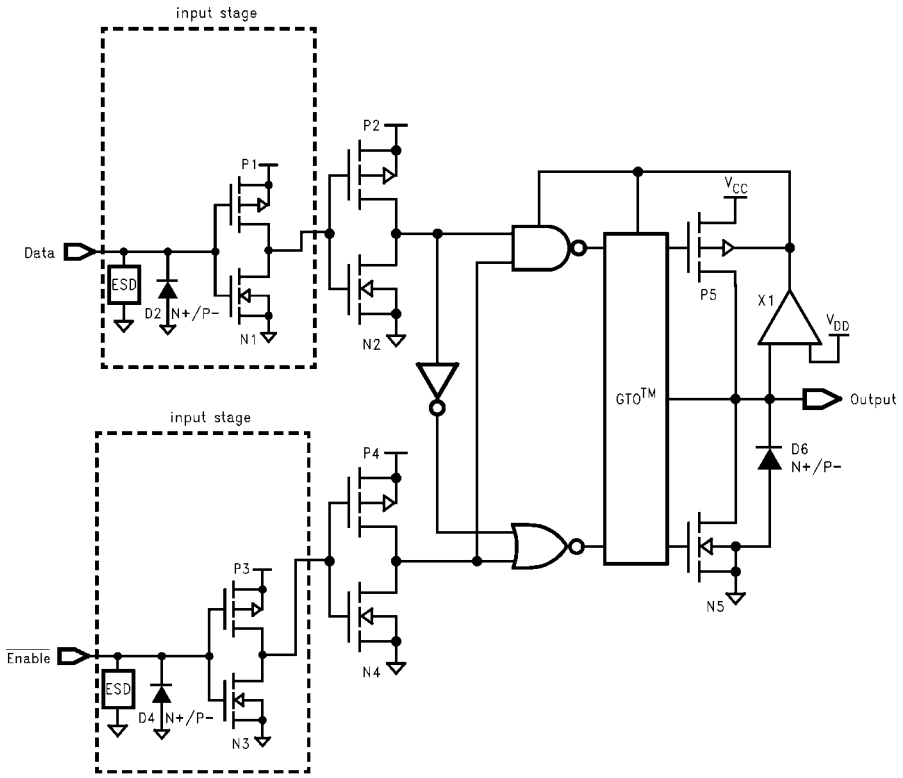


t_{rise} and t_{fall}

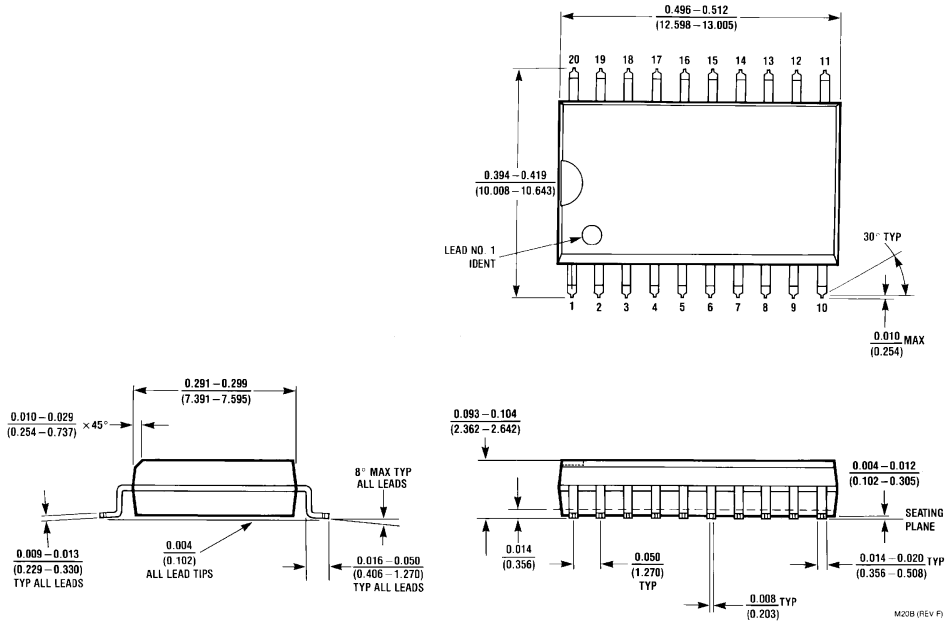
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

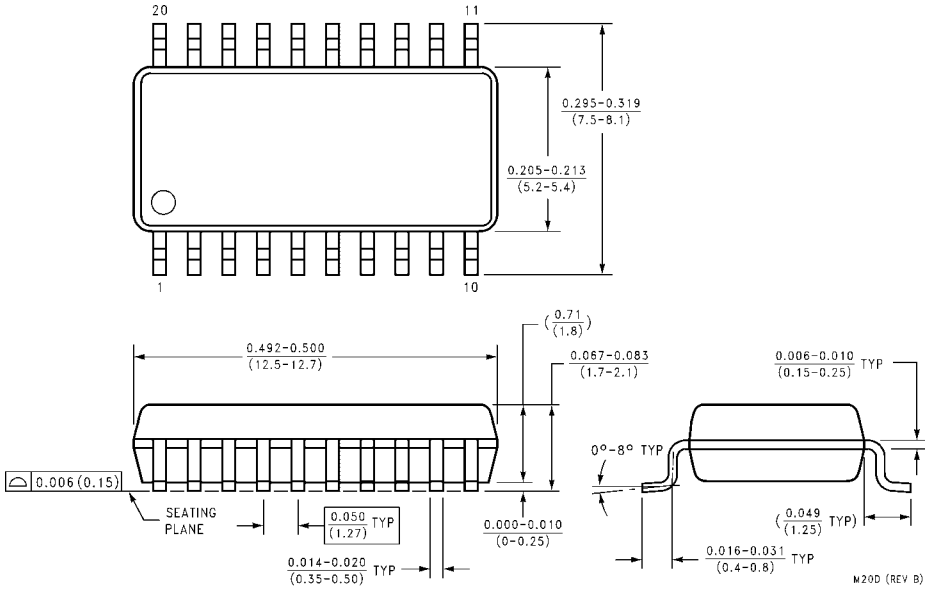
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

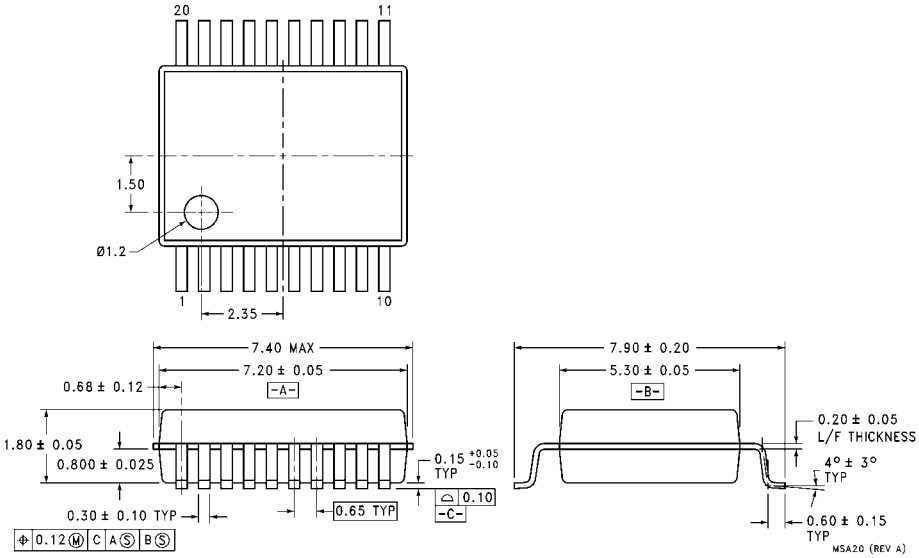


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



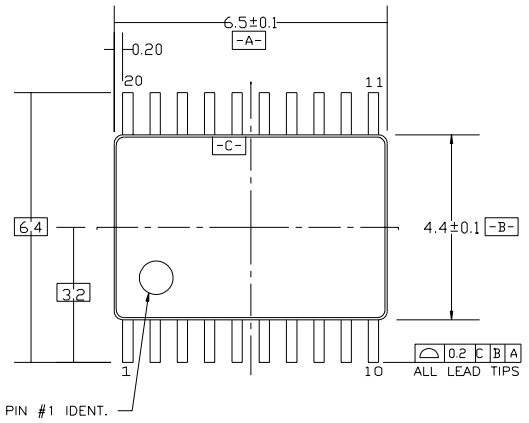
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

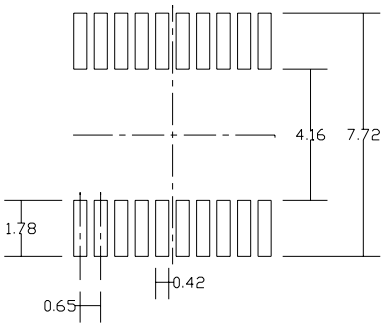
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



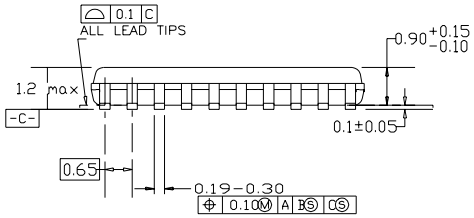
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

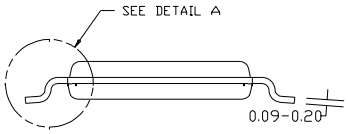
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



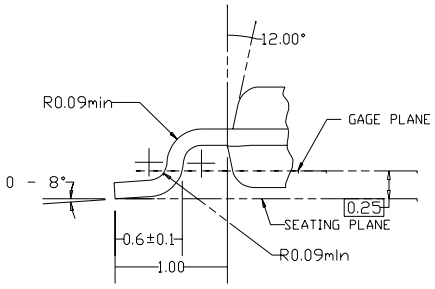


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX541
Low Voltage Octal Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX541 is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers. The LCX541 is a non inverting option of the LCX540.

This device is similar in function to the LCX244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

The LCX541 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The LCX541 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant input and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/ EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

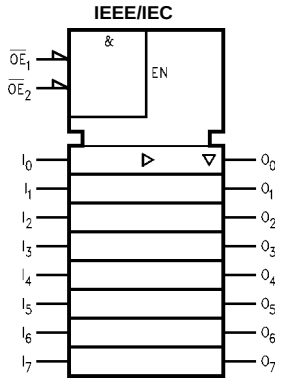
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

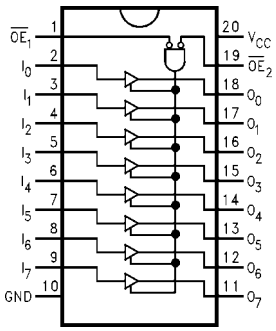
Order Number	Package Number	Package Description
74LCX541WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX541MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0, I_7	Inputs
O_0, O_7	Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	O_n
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/O's must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I, V_O ≤ 5.5V (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} = 0.6V	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.5	1.5	7.8	ns
t_{PLH}		1.5	6.5	1.5	7.5	1.5	7.8	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

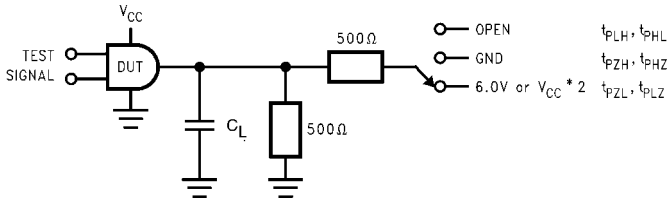
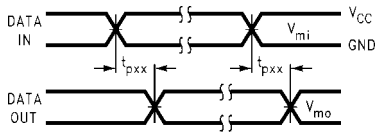
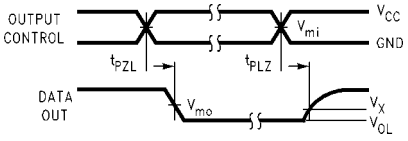


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

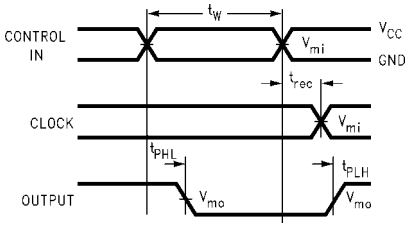
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



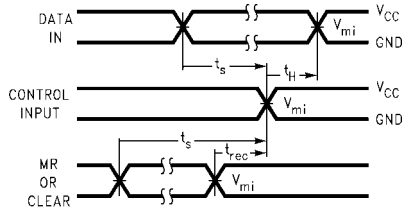
Waveform for Inverting and Non-Inverting Functions



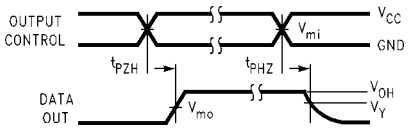
3-STATE Output Low Enable and Disable Times for Logic



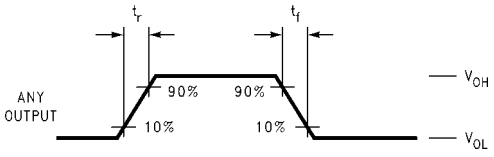
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable Times for Logic

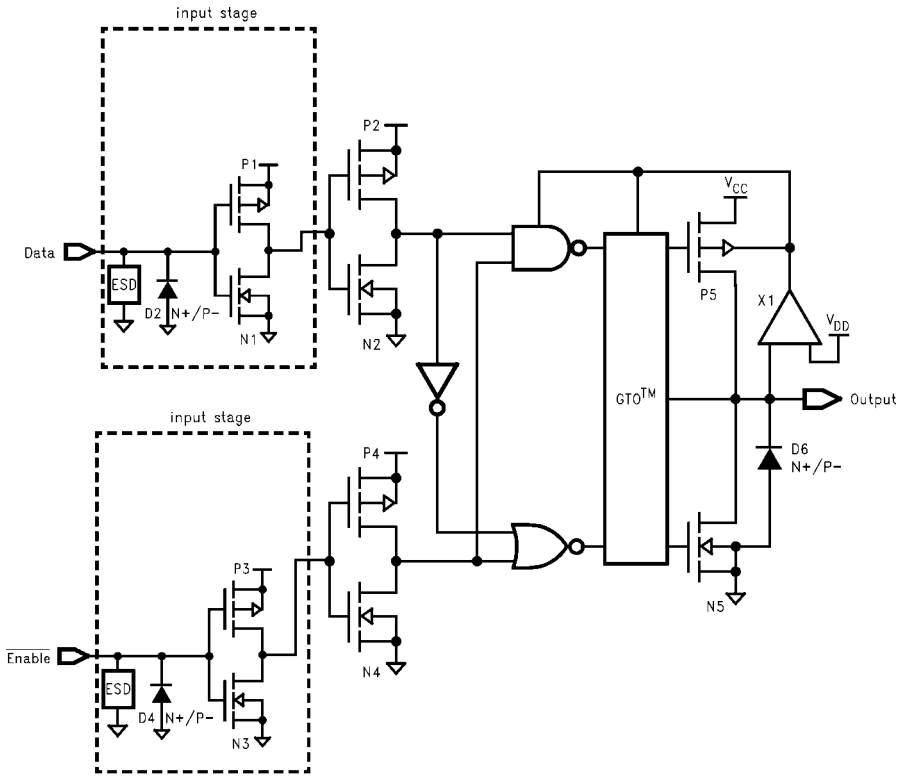


t_{rise} and t_{fall}

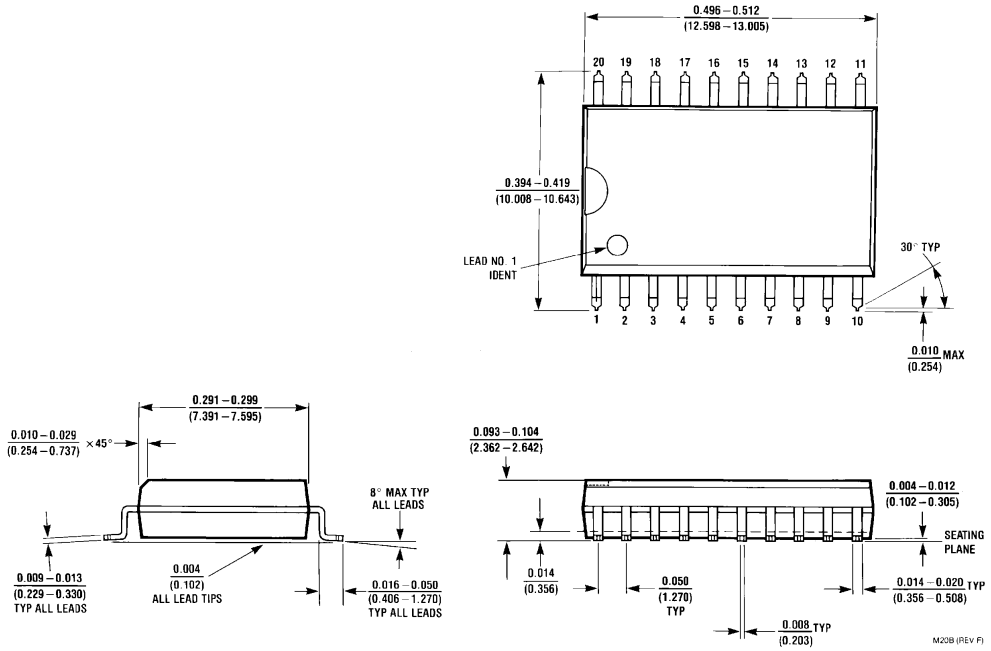
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

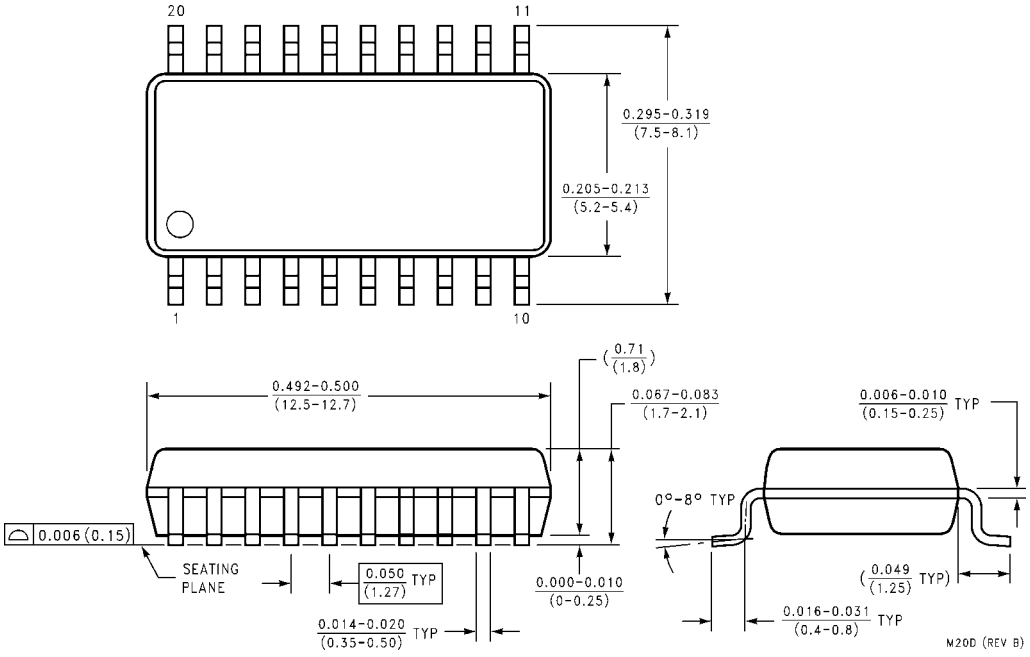
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

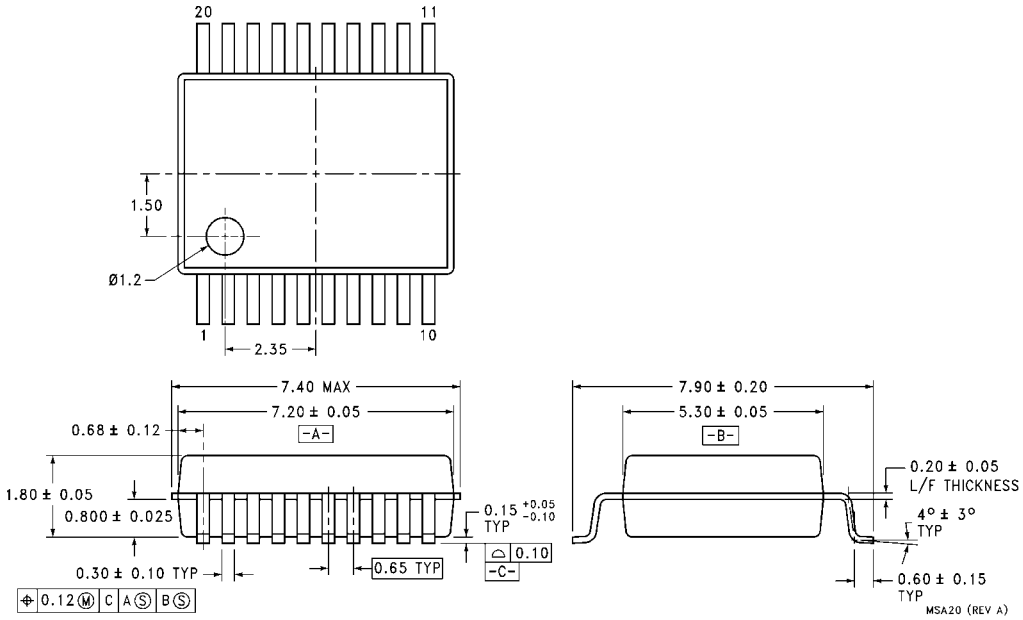


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



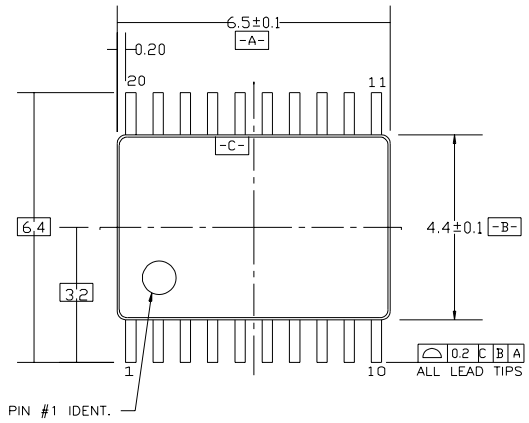
20-Lead Molded Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

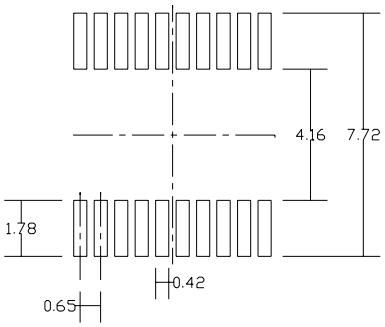
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



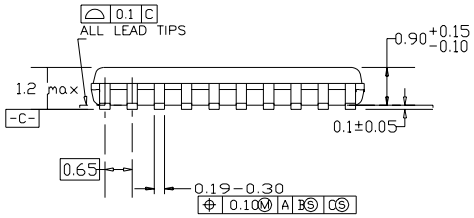
20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

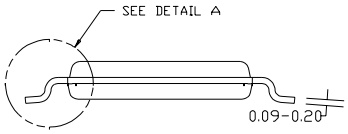
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



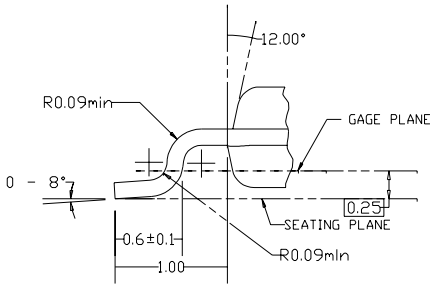


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1995
Revised April 1999

74LCX543
Low Voltage Octal Registered Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX543 is a non-inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The LCX543 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX543 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V – 3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA Output Drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

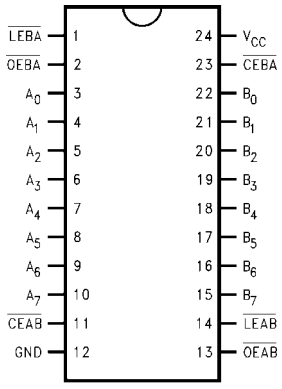
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX543WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX543MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX543MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

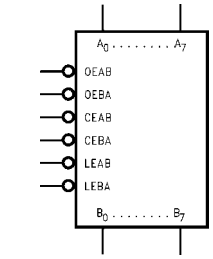
Connection Diagram



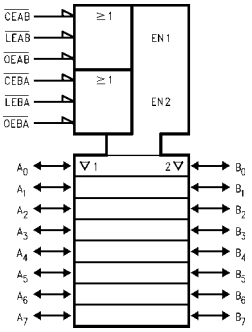
Pin Descriptions

Pin Names	Description
$\overline{OEAB}$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}$	B-to-A Latch Enable Input (Active LOW)
A_0–A_7	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B_0–B_7	B-to-A Data Inputs or A-to-B 3-STATE Outputs

Logic Symbols



IEEE/IEC



Data I/O Control Table

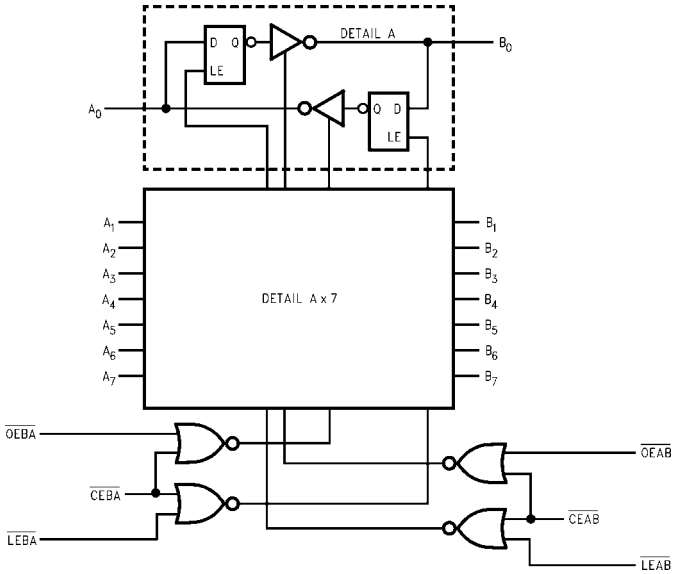
Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$

Functional Description

The LCX543 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from A_0–A_7 or take data from B_0–B_7, as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a LOW signal on the A-to-B Latch Enable ($\overline{LEAB}$) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$ inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/O's must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	$\overline{LEBA}$ to A_n or $\overline{LEAB}$ to B_n	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	9.0	1.5	10.0	1.5	11.0	ns
t_{PZH}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.5	9.0	1.5	10.0	1.5	11.0	
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n							
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	7.5	1.5	8.4	ns
t_{PHZ}	$\overline{OEBA}$ or $\overline{OEAB}$ to A_n or B_n	1.5	7.0	1.5	7.5	1.5	8.4	
	$\overline{CEBA}$ or $\overline{CEAB}$ to A_n or B_n							
t_S	Setup Time, HIGH or LOW Data to $\overline{LEXX}$	2.5		2.5		4.0		ns
t_H	Hold Time, HIGH or LOW Data to $\overline{LEXX}$	1.5		1.5		2.0		ns
t_W	Pulse Width, Latch Enable, LOW	3.3		3.3		3.3		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 6)		1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

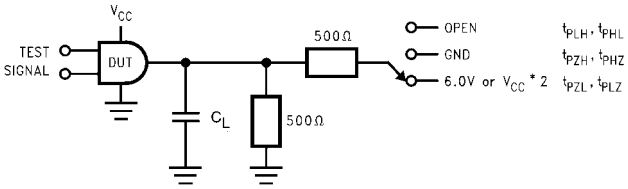
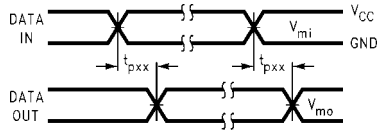
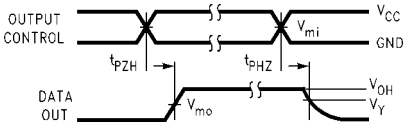


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

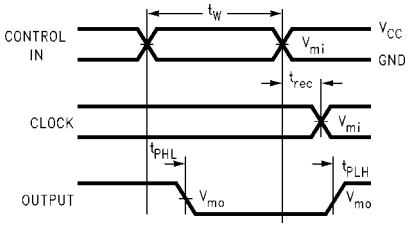
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



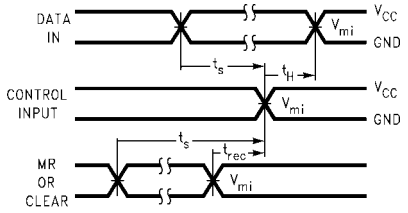
Waveform for Inverting and Non-Inverting Functions



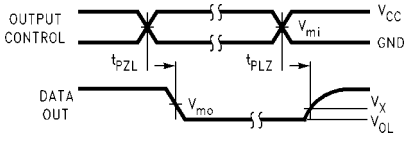
3-STATE Output High Enable and Disable Times for Logic



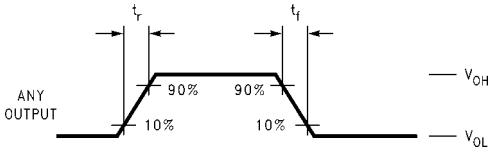
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

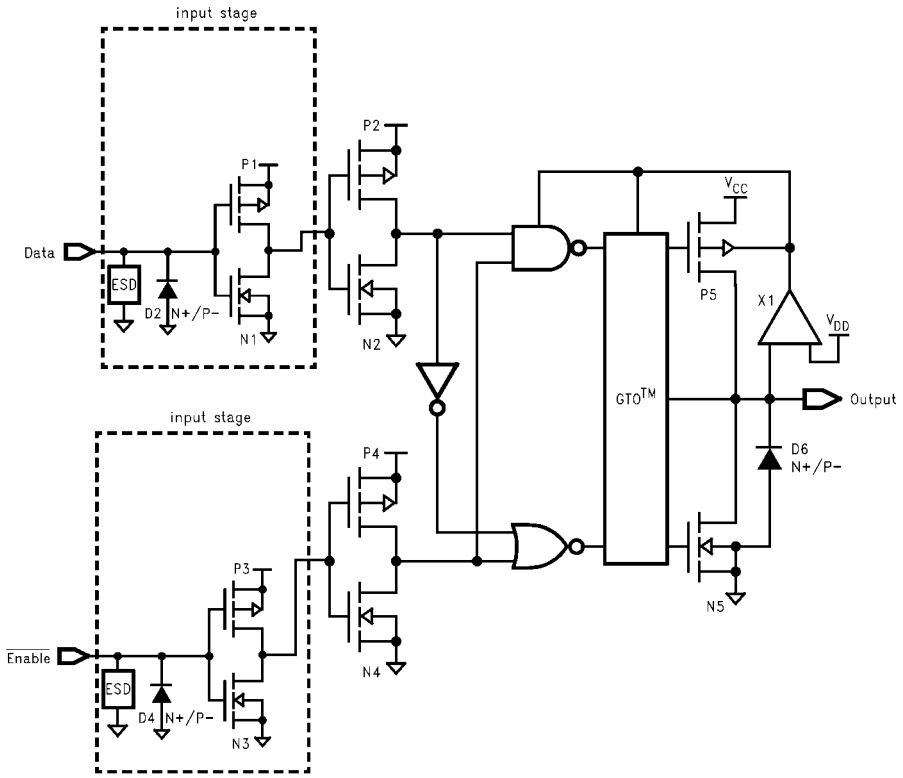


t_{rise} and t_{fall}

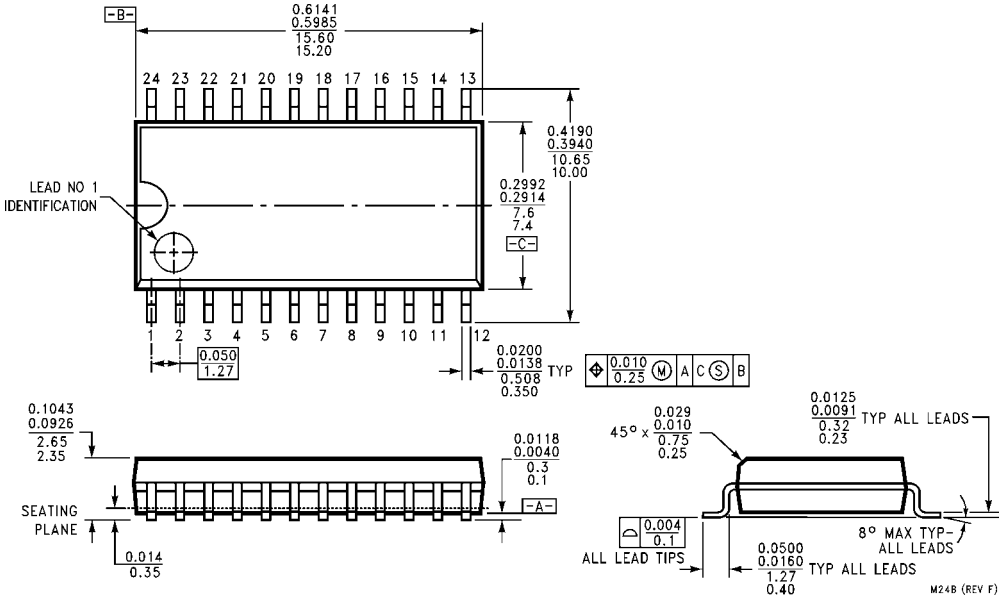
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

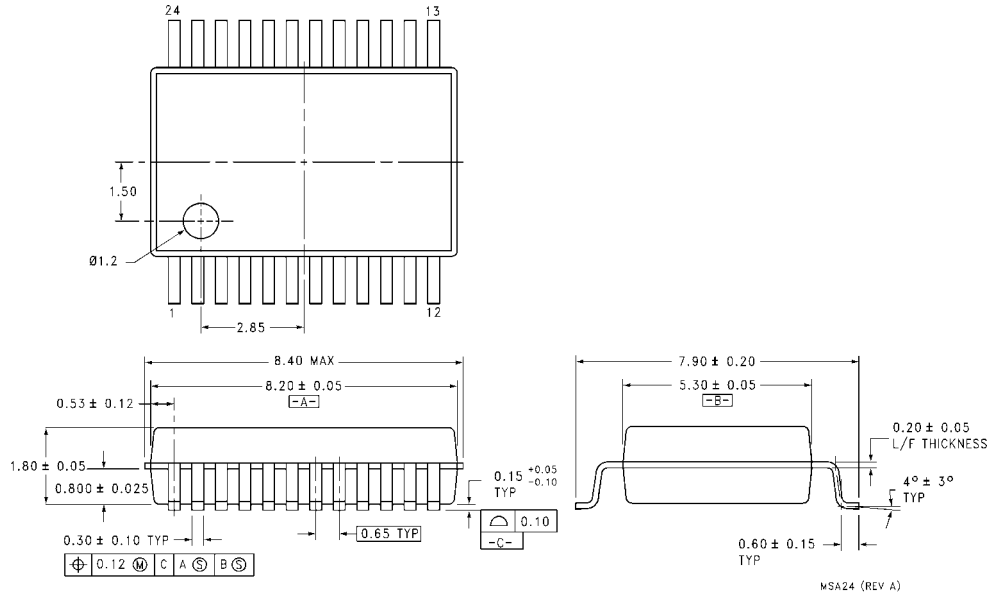
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

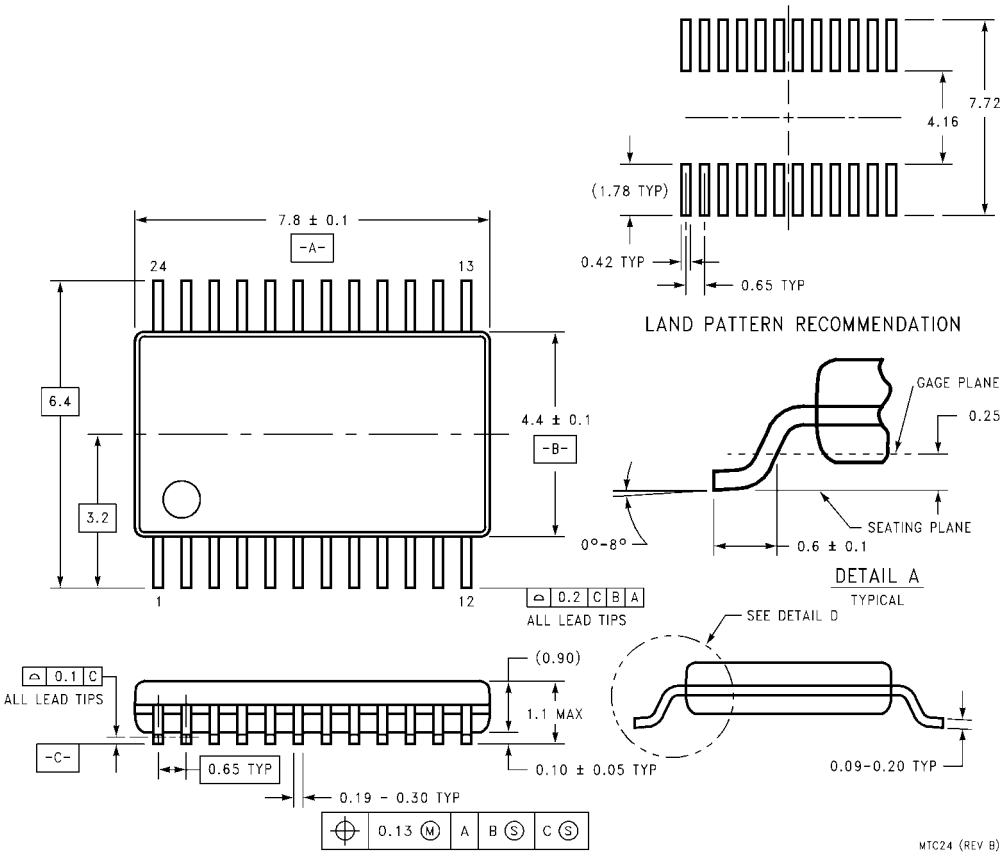


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX573
Low Voltage Octal Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

The LCX573 is functionally identical to the LCX373 but has inputs and outputs on opposite sides.

The LCX573 is designed for low voltage (3.3V or 2.5V) applications with capability of interfacing to a 5V signal environment. The LCX573 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 200V

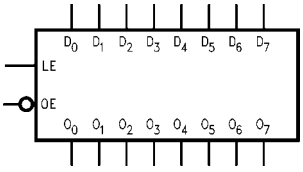
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

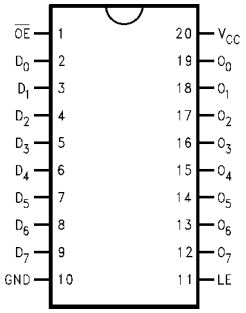
Order Number	Package Number	Package Description
74LCX573WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX573SJ	M20D	20-Lead Molded Small Outline (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX573MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Functional Description

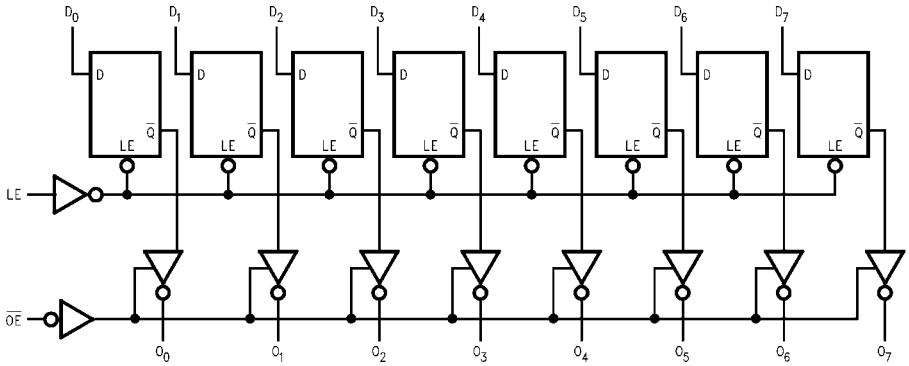
The LCX573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage
L = LOW Voltage
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 − 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	μA
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5 \pm 0.2V$		
		$C_L = 50pF$		$C_L = 50pF$		$C_L = 30pF$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	8.0	1.5	9.0	1.5	9.6	ns
t_{PLH}	D_n to O_n	1.5	8.0	1.5	9.0	1.5	9.6	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	LE to O_n	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_S	Setup Time, D_n to LE	2.5		2.5		4.0		ns
t_H	Hold Time, D_n to LE	1.5		1.5		2.0		ns
t_W	LE Pulse Width	3.3		3.3		4.0		ns
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

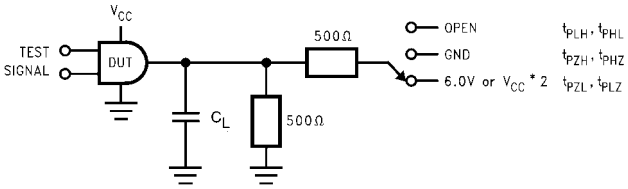
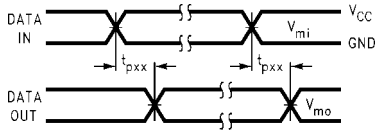
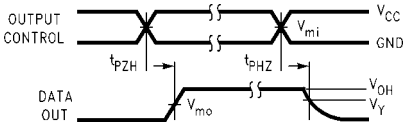


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

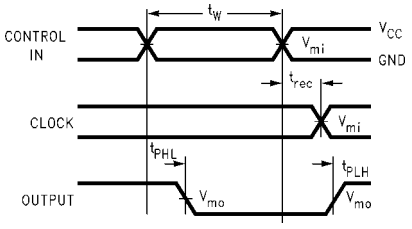
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



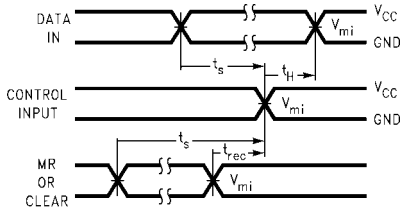
Waveform for Inverting and Non-Inverting Functions



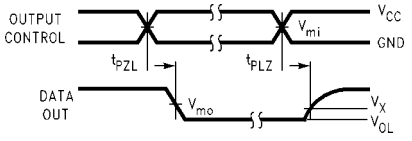
3-STATE Output High Enable and Disable Times for Logic



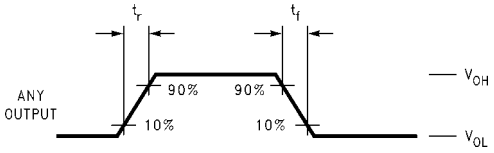
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

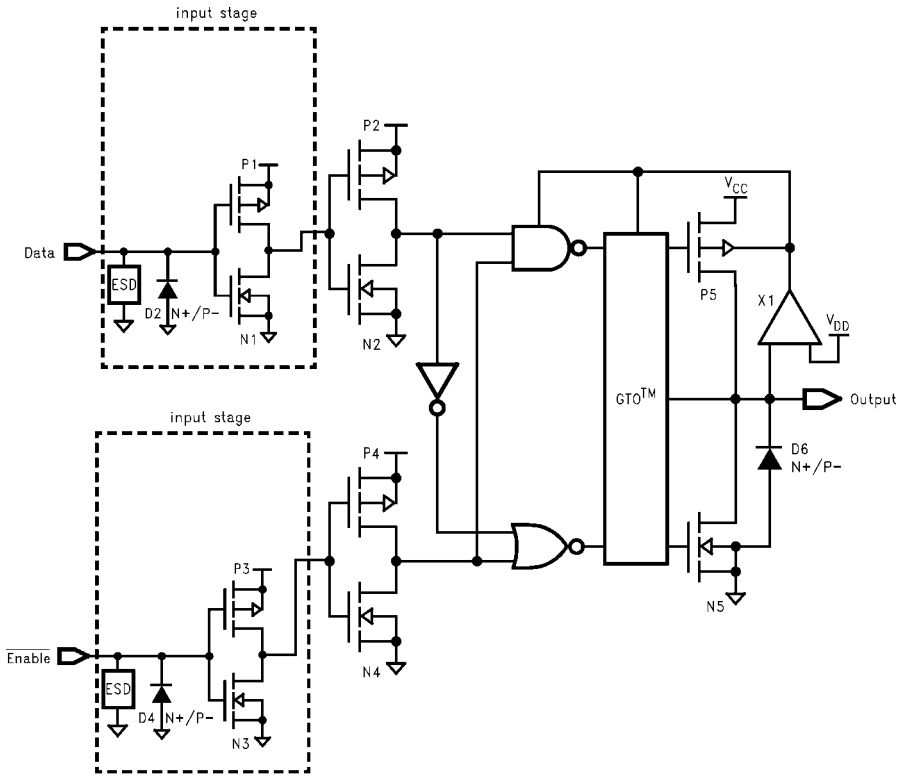


t_{rise} and t_{fall}

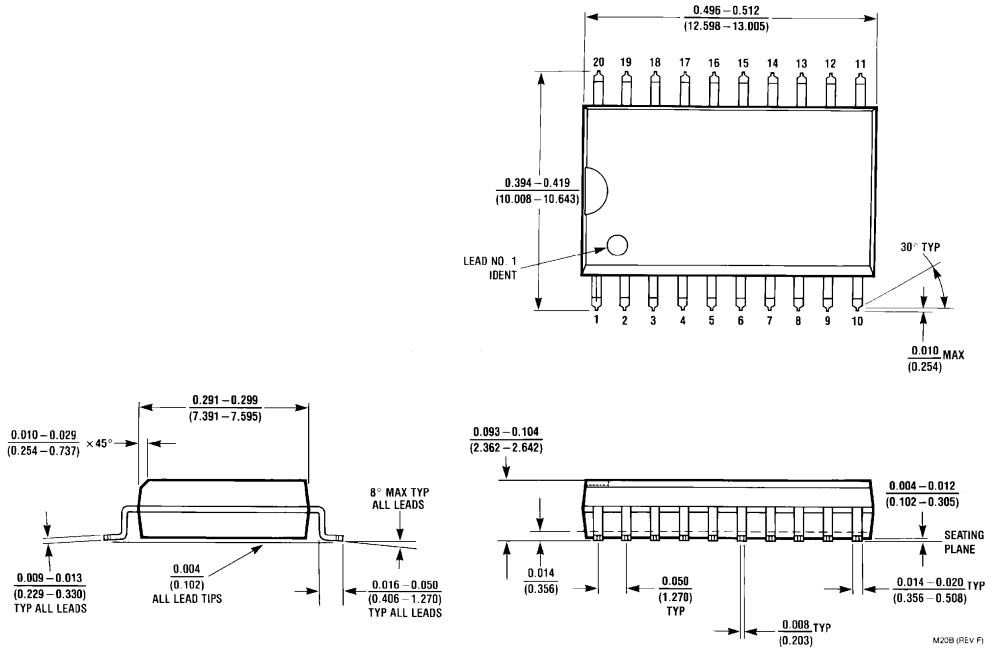
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

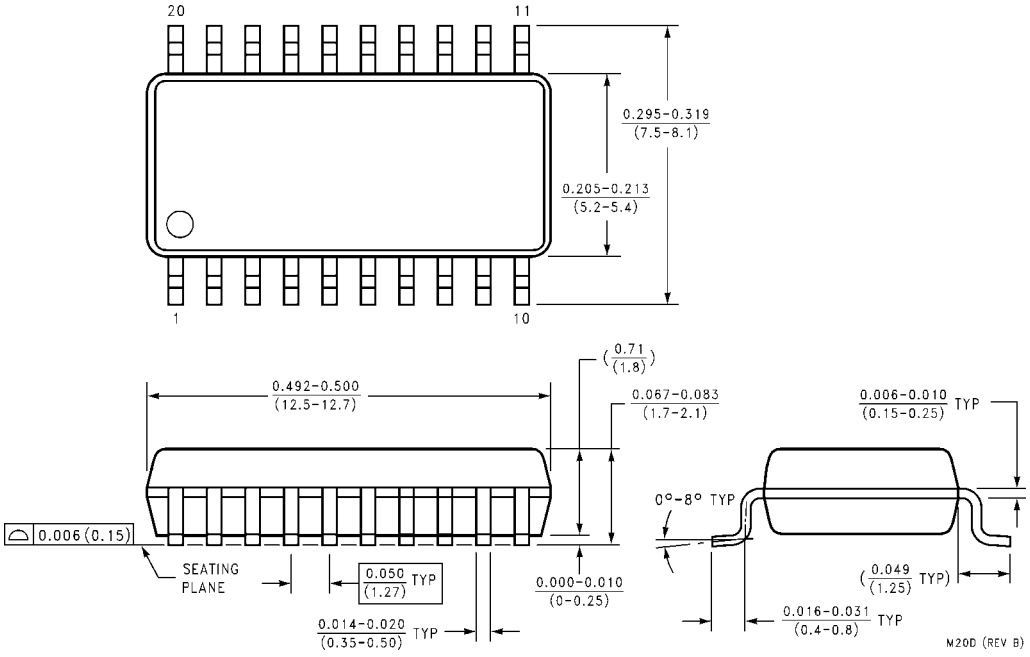
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

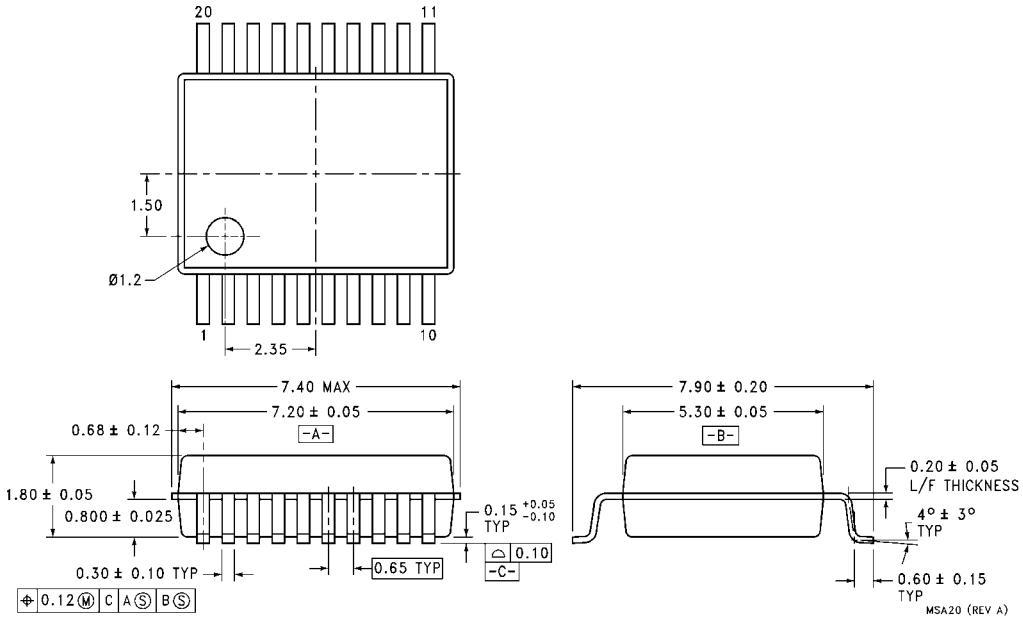


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



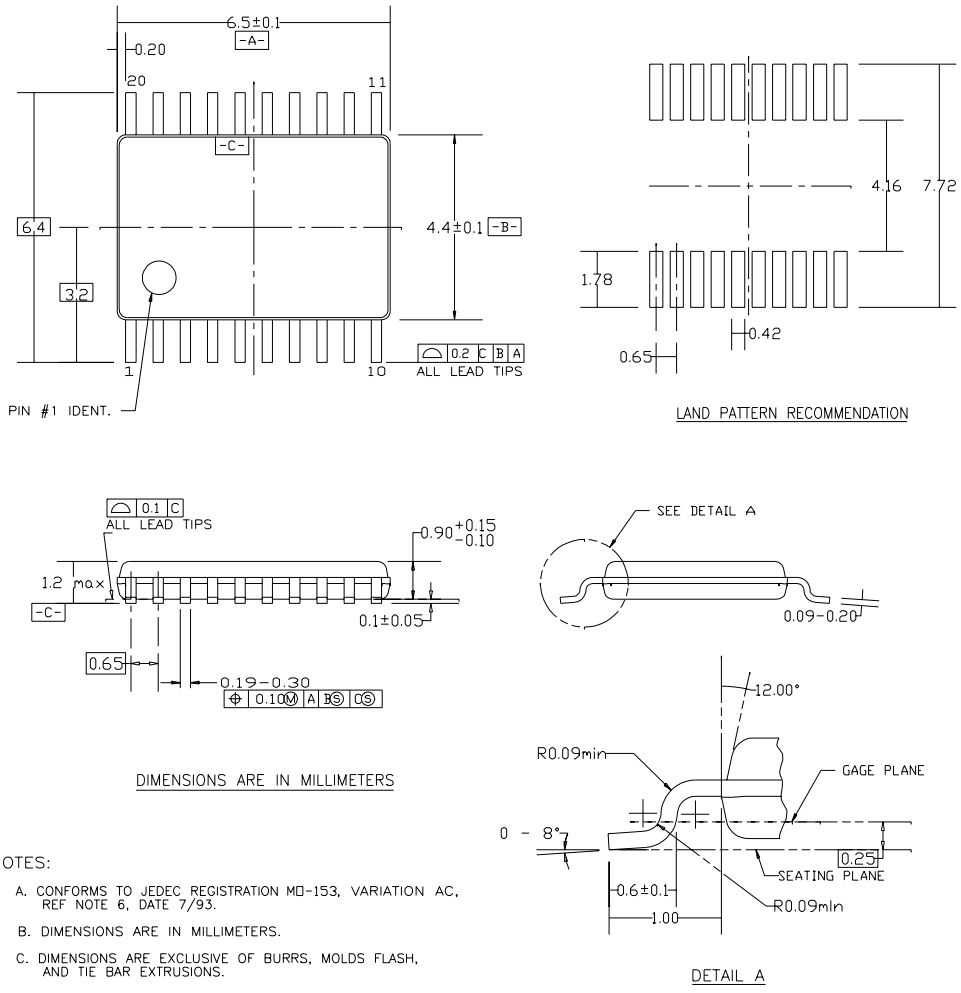
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX574

Low Voltage Octal D-Type Flip-Flop with 5V Tolerant Inputs and Outputs

General Description

The LCX574 is a high-speed, low power octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable ($\overline{OE}$). The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The LCX574 is functionally identical to the LCX374 except for the pinouts.

The LCX574 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The LCX574 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.5 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

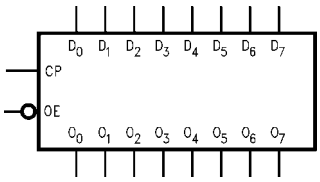
Note 1: To Ensure the high-Impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

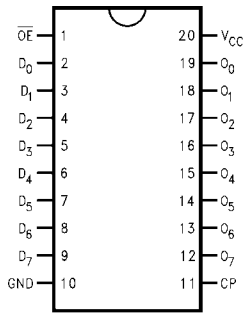
Order Number	Package Number	Package Description
74LCX574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX574MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

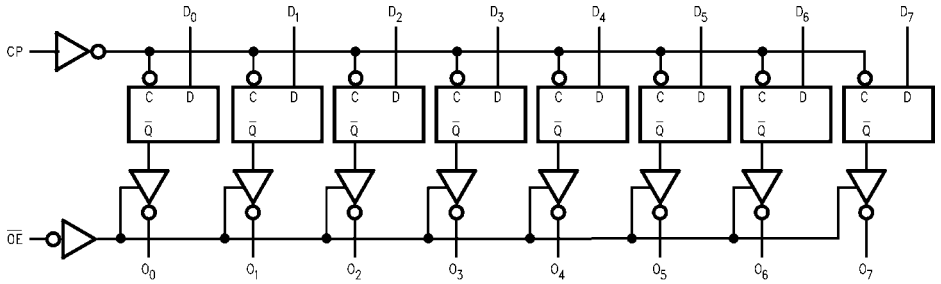
The LCX574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O_n	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	⌐	L	L	Z	Load
H	⌐	H	H	Z	Load
L	⌐	L	L	L	Data Available
L	⌐	H	H	H	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = − 8mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	μA
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5 \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150						MHz
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	CP to O_n	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_S	Setup Time	2.5		2.5		4.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.3		3.3		4.0		ns
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

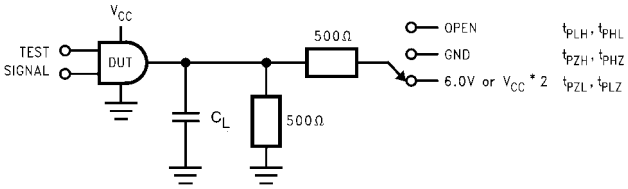
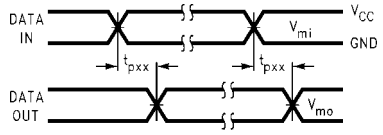
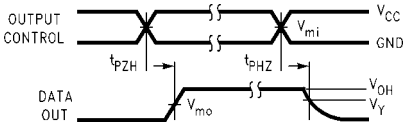


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

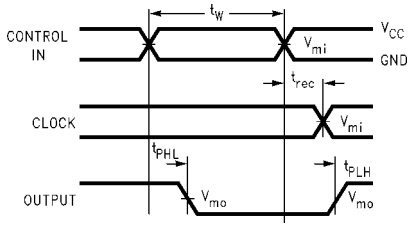
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



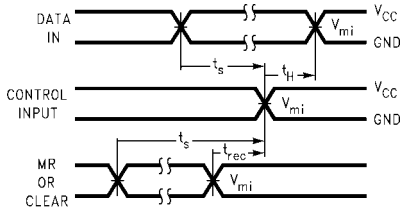
Waveform for Inverting and Non-Inverting Functions



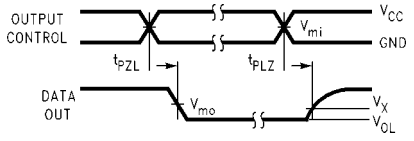
3-STATE Output High Enable and Disable Times for Logic



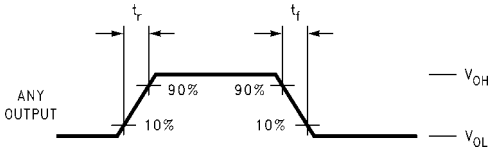
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

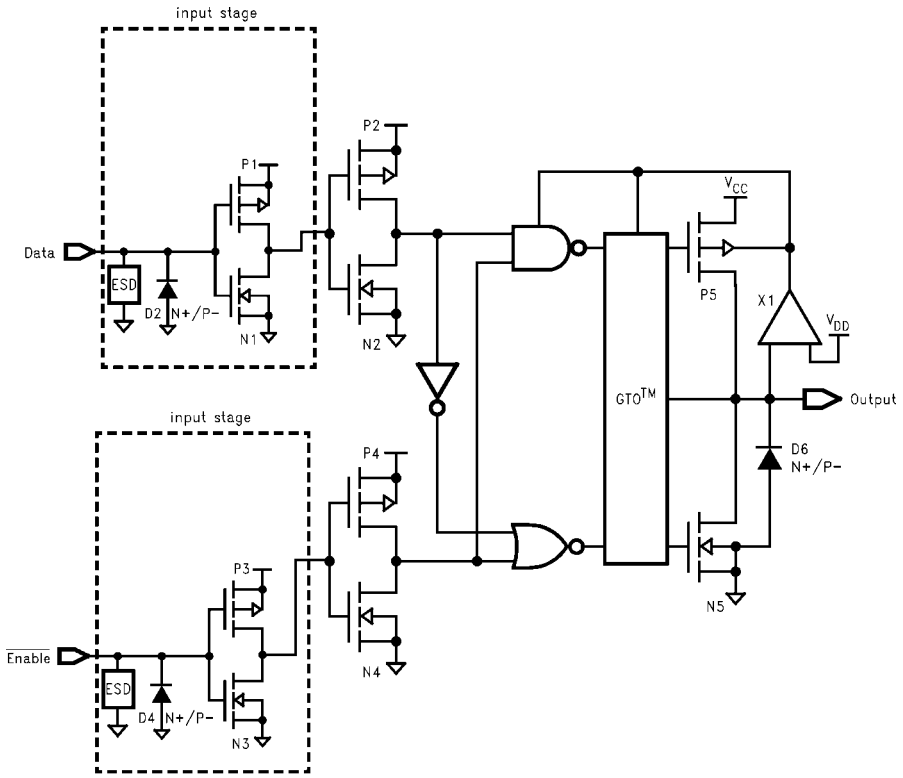


t_{rise} and t_{fall}

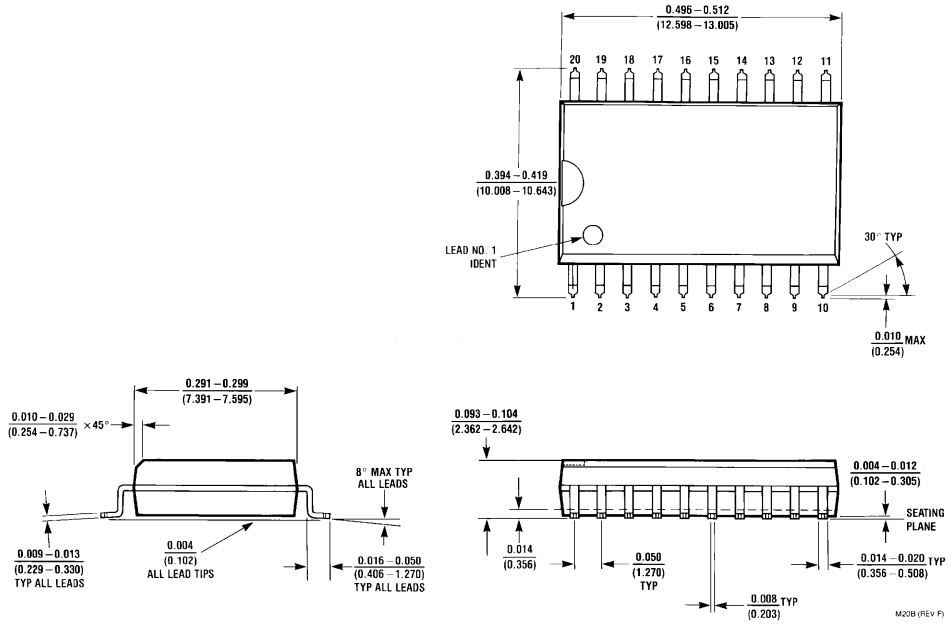
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

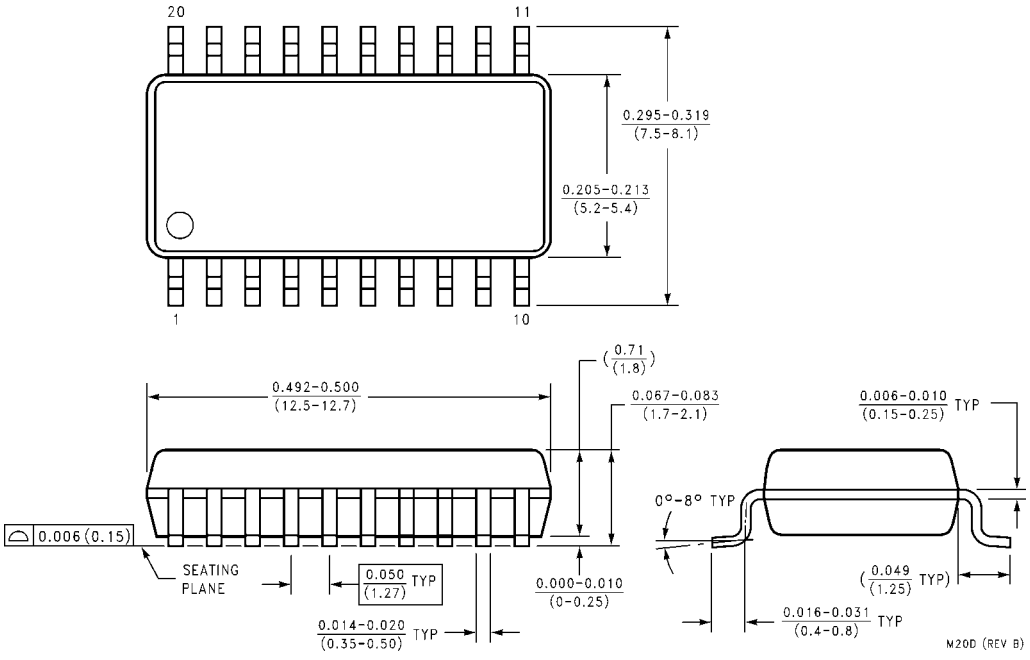
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

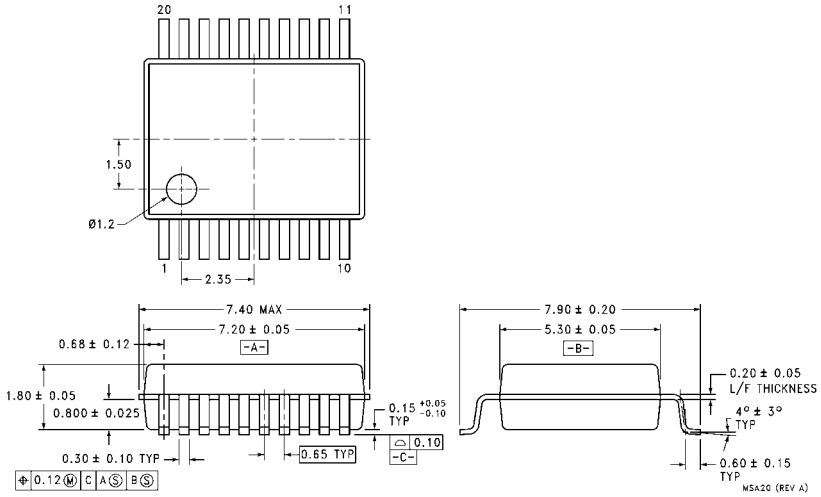


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



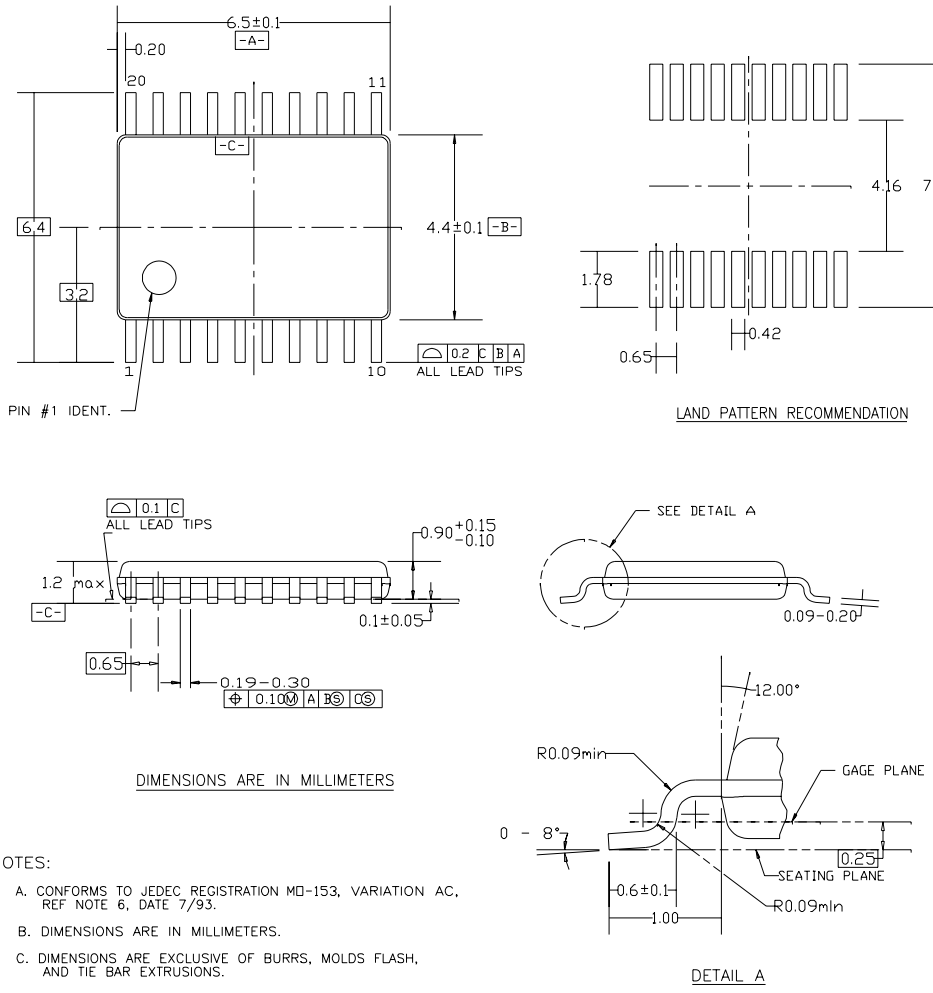
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised April 1999

74LCX646
Low Voltage Octal Transceiver/Register with 5V Tolerant Inputs and Outputs

General Description

The LCX646 consists of registered bus transceiver circuits, D-type flip-flops, and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate pin (CPAB or CPBA)(see Functional Description).

The LCX646 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX646 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V – 3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

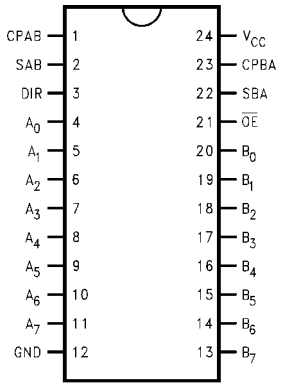
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX646WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX646MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX646MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

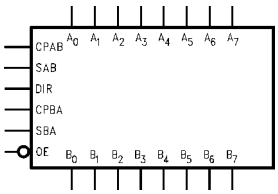
Connection Diagram

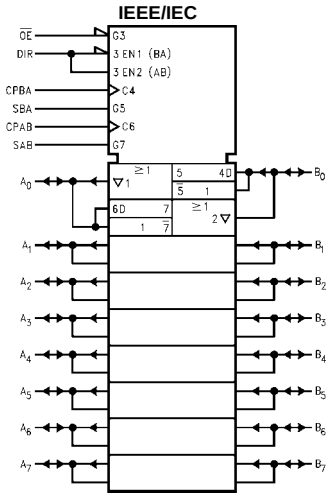


Pin Descriptions

Pin Names	Description
A_0–A_7	Data Register A Inputs
	Data Register A Outputs
B_0–B_7	Data Register B Inputs
	Data Register B Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
$\overline{OE}$	Output Enable Input
DIR	Direction Control Input

Logic Symbols





Truth Table

(Note 2)

Inputs						Data I/O		Function
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↑ = LOW-to-HIGH Transition

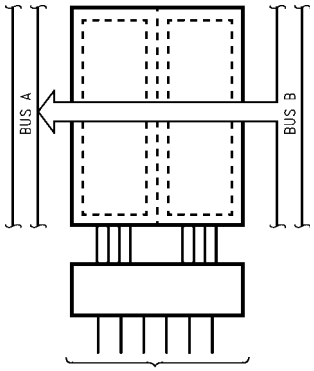
Note 2: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

Functional Description

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both. The select (SAB, SBA) controls can multiplex stored and real-time. The examples shown below demonstrate the four fundamental bus-management functions that can be performed.

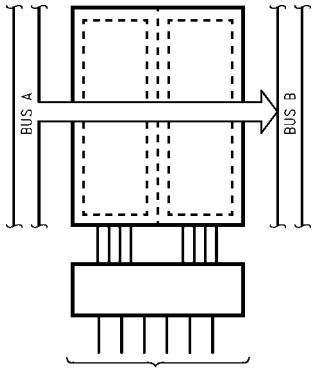
The direction control (DIR) determines which bus will receive data when $\overline{OE}$ is LOW. In the isolation mode ($\overline{OE}$ HIGH), A data may be stored in one register and/or B data may be stored in the other register. When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two busses, A or B, may be driven at a time.

Real-Time Transfer
Bus B to Bus A



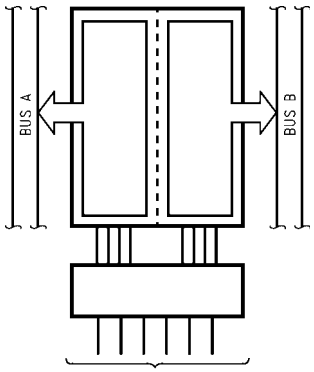
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Real-Time Transfer
Bus A to Bus B



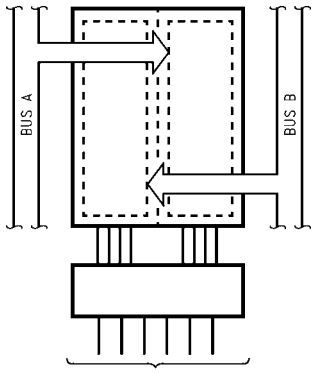
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	X	X	L	X

Transfer Storage
Data to A or B



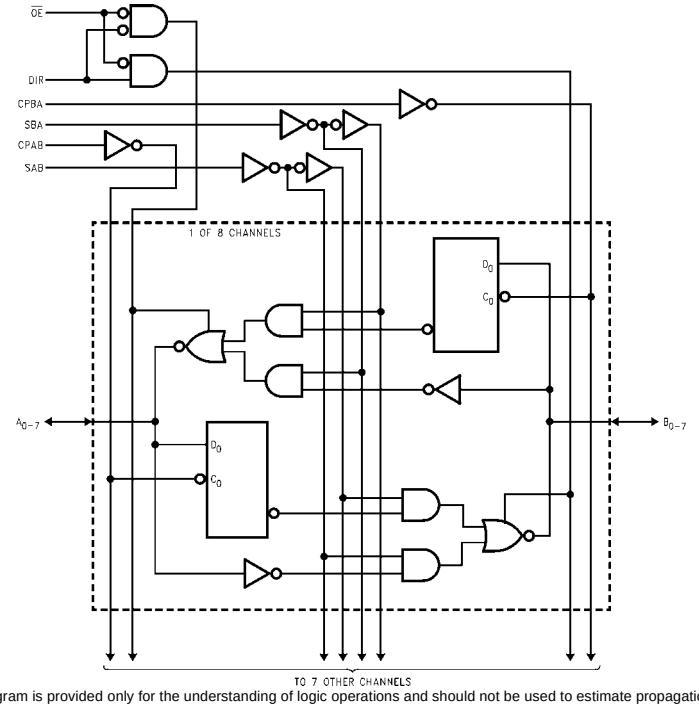
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	H or L	X	H
L	H	H or L	X	H	X

Storage



$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	↑	X	L	X
L	L	X	↑	X	L
H	X	↑	X	X	X
H	X	X	↑	X	X

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 4)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused inputs or I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V	2.3 − 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	µA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 6)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150						MHz
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	Bus to Bus	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	Clock to Bus	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	Select to Bus	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PHZ}		1.5	8.5	1.5	9.5	1.5	10.5	
t_S	Setup Time	2.5		2.5		4.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.3		3.3		4.0		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 7)		1.0					

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

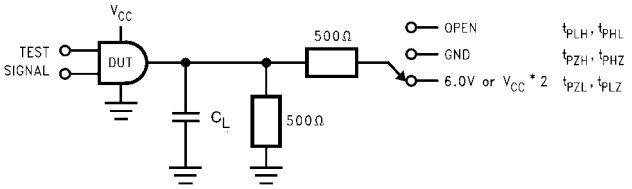
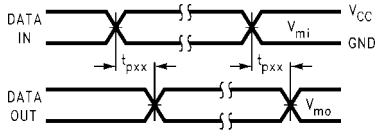
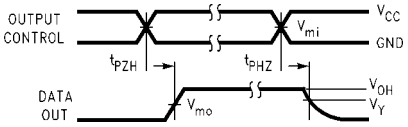


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

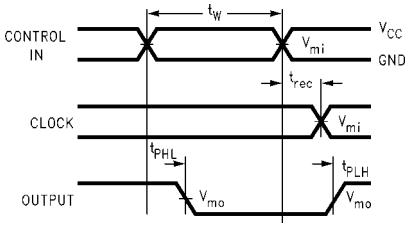
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



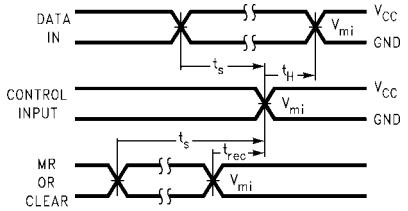
Waveform for Inverting and Non-Inverting Functions



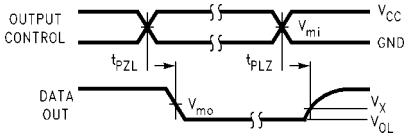
3-STATE Output High Enable and Disable Times for Logic



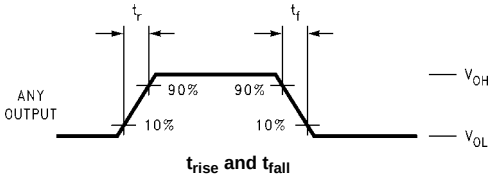
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

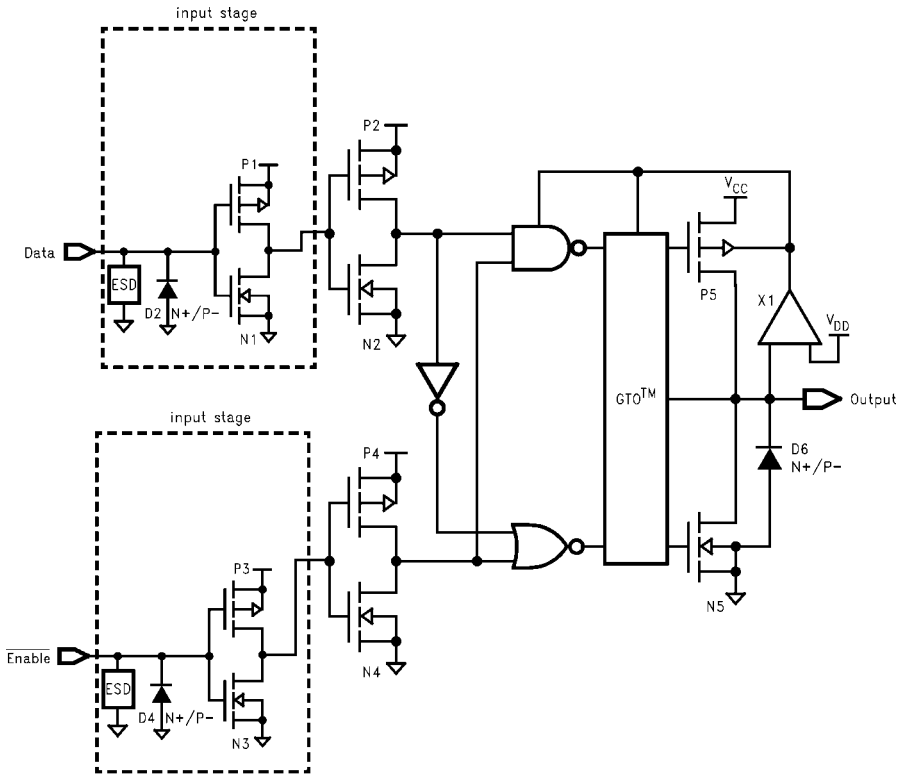


t_{rise} and t_{fall}

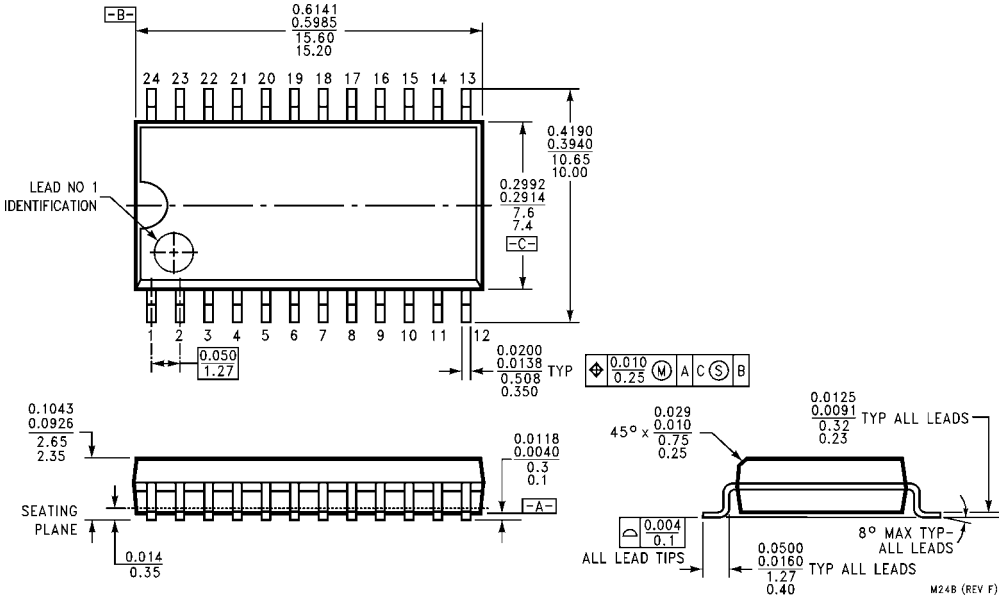
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

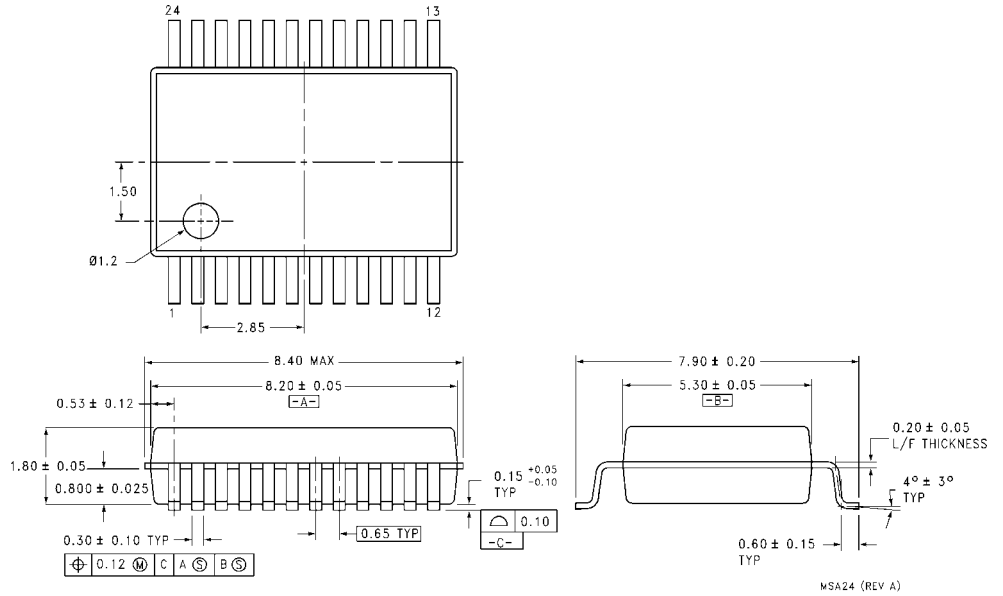
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

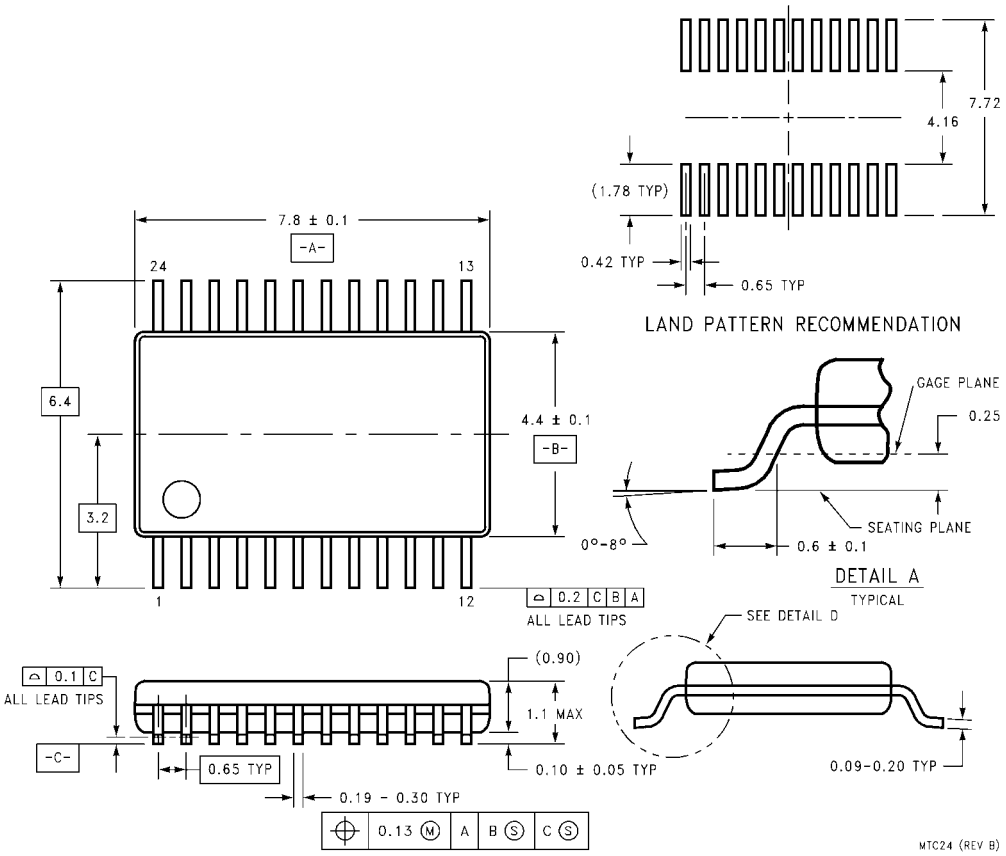


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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February 1994
Revised April 1999

74LCX652
Low Voltage Transceiver/Register with 5V Tolerant Inputs and Outputs

General Description

The LCX652 consists of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to the HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function.

The LCX652 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX652 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V – 3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

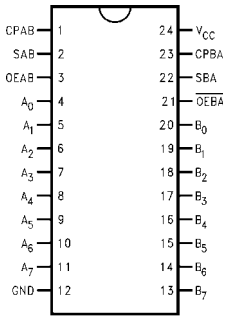
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX652WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX652MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX652MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

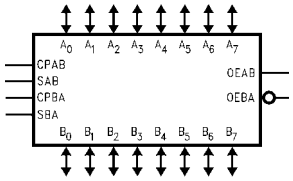
Connection Diagram



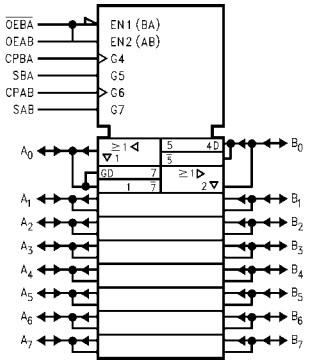
Pin Descriptions

Pin Names	Description
A_0–A_7, B_0–B_7	A and B Inputs/3-STATE Outputs
CPAB, CPBA	Clock Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{OEBA}$	Output Enable Inputs

Logic Symbols



IEEE/IEC



Truth Table

(Note 2)

Inputs						Inputs/Outputs		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Note 2: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs.

Functional Description

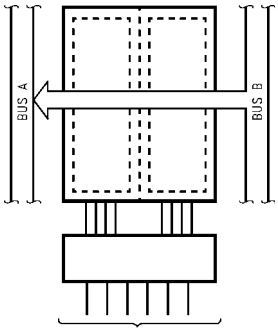
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples below demonstrate the four fundamental bus-management functions that can be performed with the Octal bus transceiver and receiver.

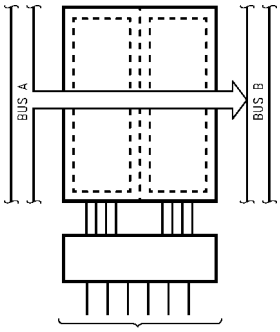
Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB and $\overline{\text{OEBA}}$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Real-Time Transfer
Bus B to Bus A



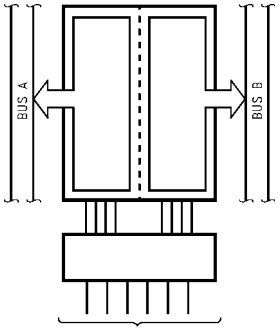
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Real-Time Transfer
Bus A to Bus B



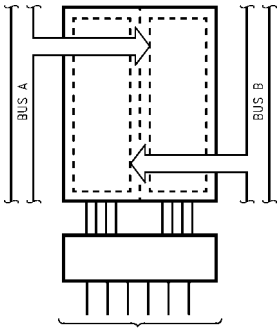
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

Transfer Storage
Data to A or B



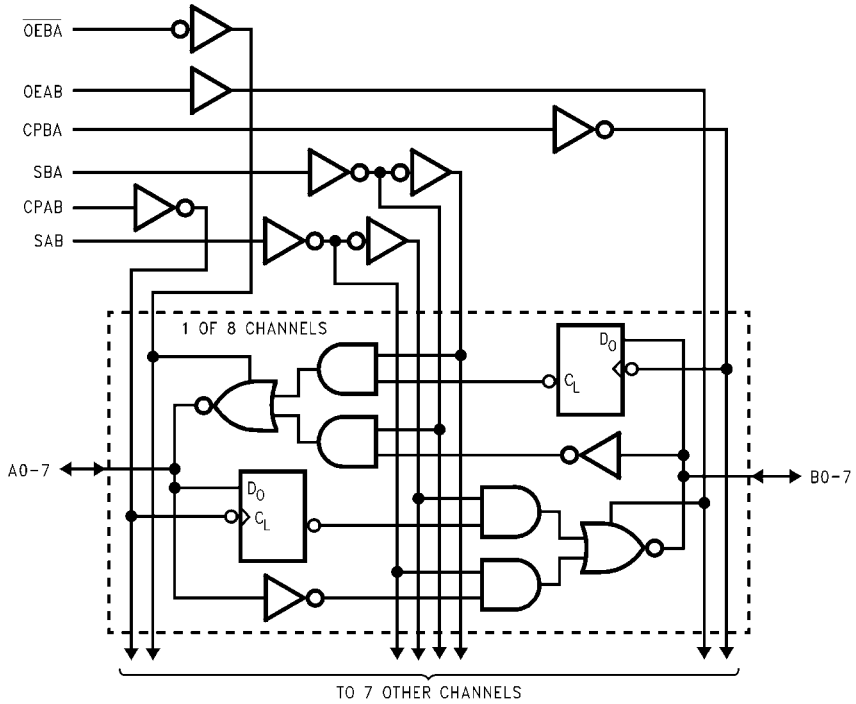
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

Storage



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
X	H	⌐	X	X	X
L	X	X	⌐	X	X
L	H	⌐	⌐	X	X

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 4)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused inputs or I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 − 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	µA
I_{OZ}	3-STATE I/O Leakage	0 ≤ V_O ≤ 5.5V V_I = V_{IH} or V_{IL}	2.3 − 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 6)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$; $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150						MHz
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	Bus to Bus	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	Clock to Bus	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PLH}	Select to Bus	1.5	8.5	1.5	9.5	1.5	10.5	
t_{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	
t_{PLZ}	Output Disable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t_{PHZ}		1.5	8.5	1.5	9.5	1.5	10.5	
t_S	Setup Time	2.5		2.5		4.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width	3.3		3.3		4.0		ns
t_{OSHL}	Output to Output Skew (Note 7)		1.0					ns
t_{OSLH}			1.0					

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

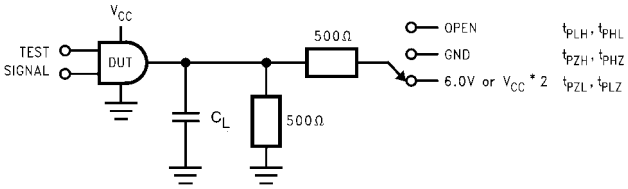
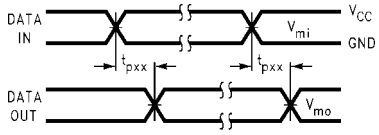
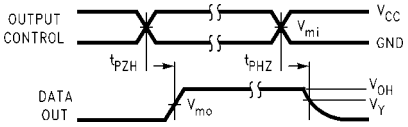


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

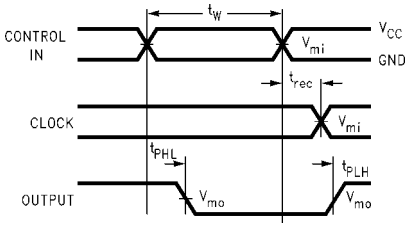
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



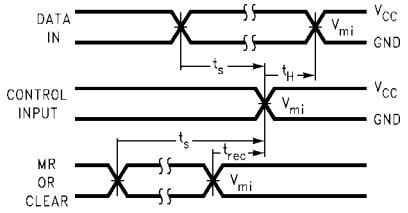
Waveform for Inverting and Non-Inverting Functions



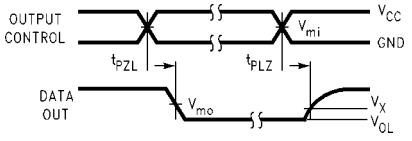
3-STATE Output High Enable and Disable Times for Logic



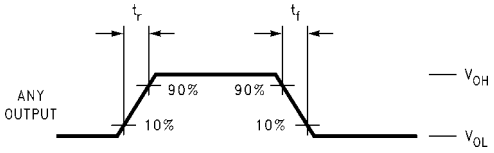
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

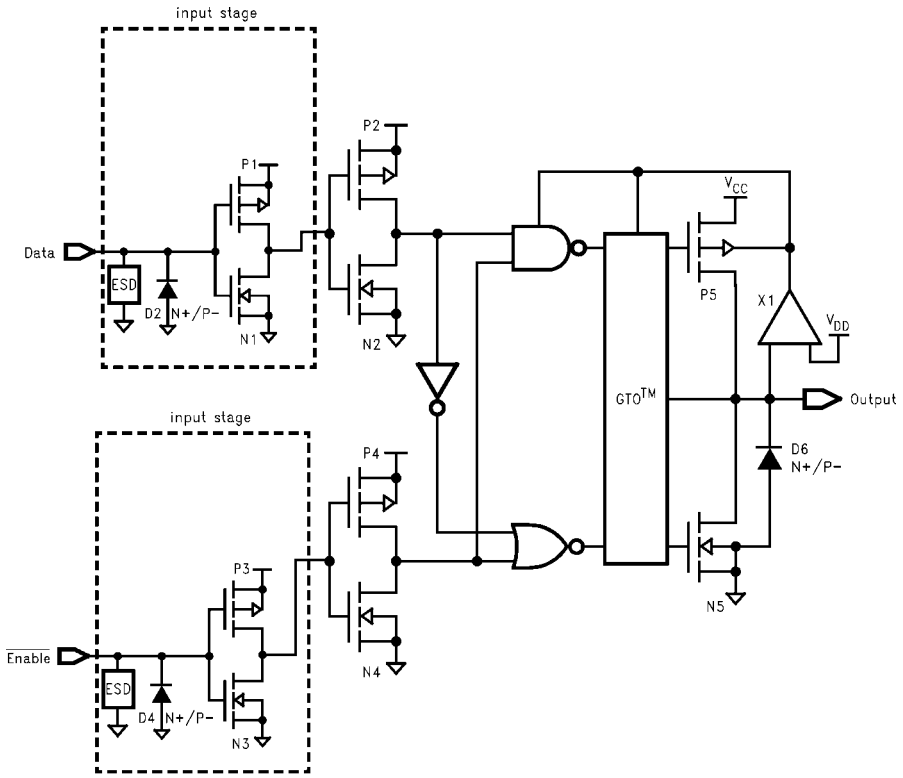


t_{rise} and t_{fall}

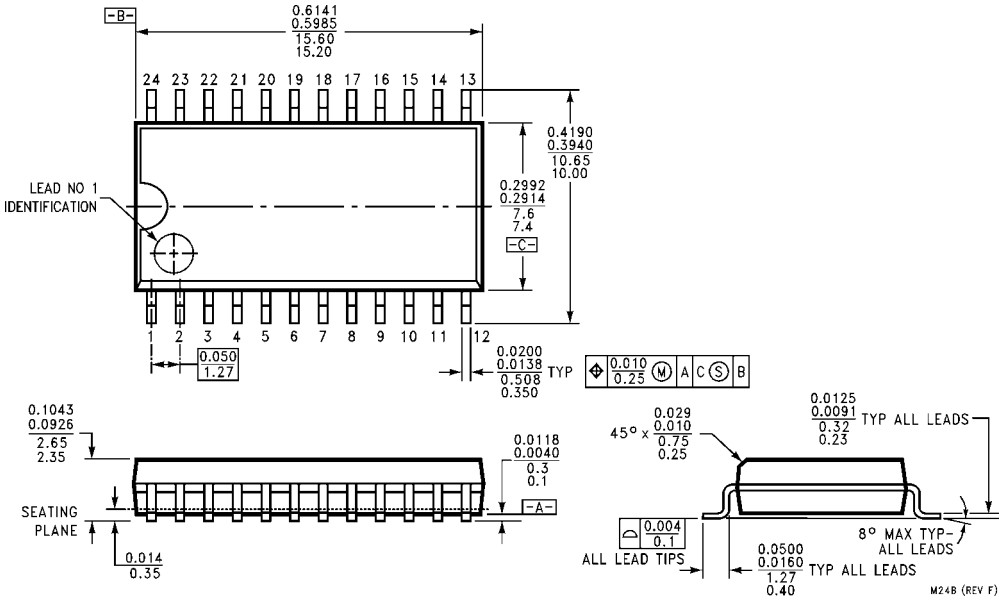
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

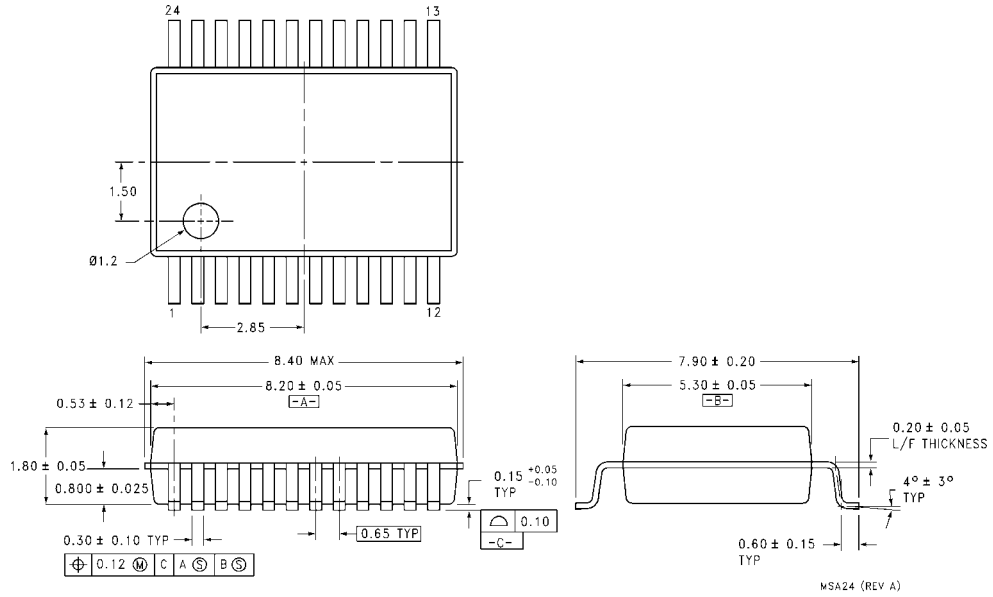
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

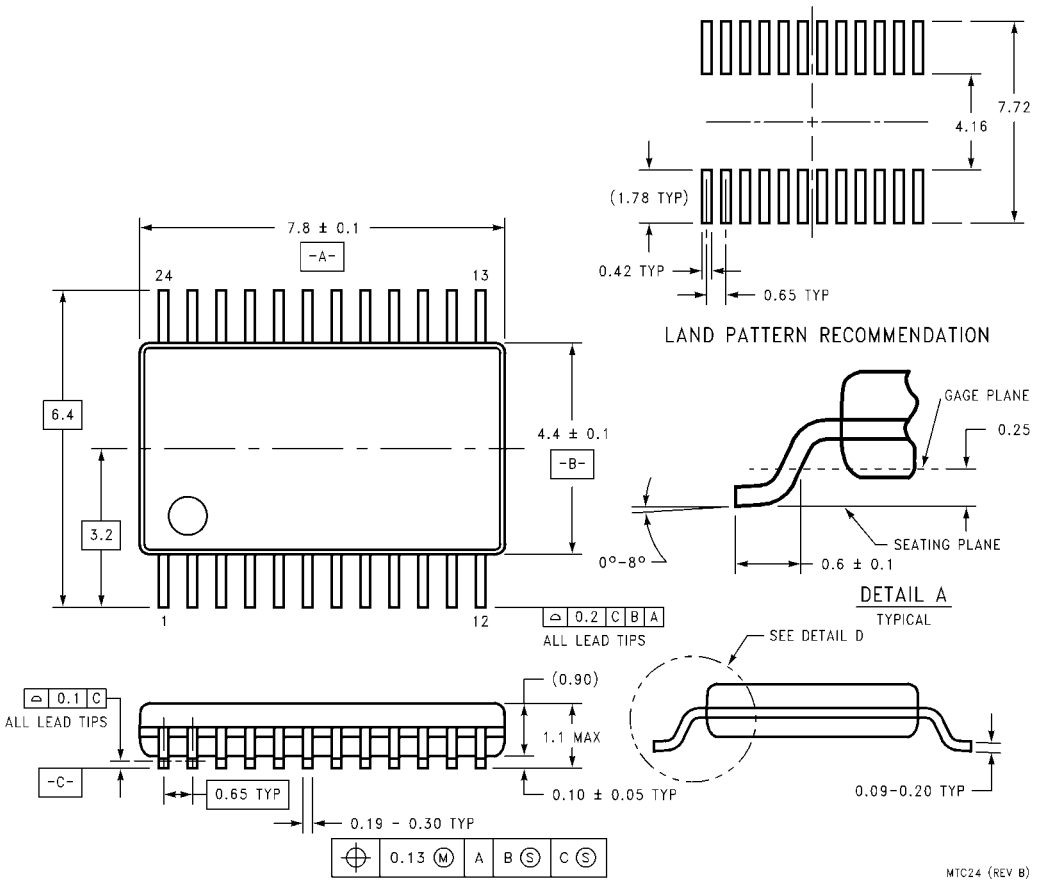


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised April 1999

74LCX74
Low Voltage Dual D-Type Positive Edge-Triggered Flip-Flop with 5V Tolerant Inputs

General Description

The LCX74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

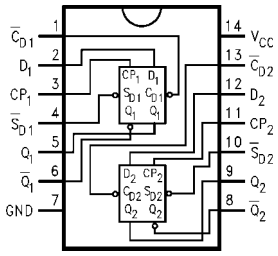
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description
74LCX74M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX74MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

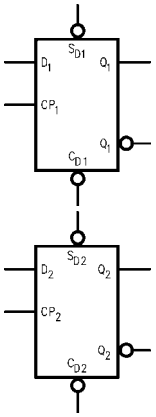
Connection Diagram



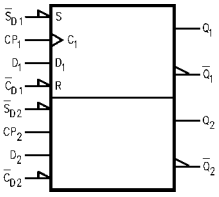
Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

Logic Symbols



IEEE/IEC



Truth Table

(Each Half)

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	↗	H	H	L
H	H	↗	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
↗ = LOW-to-HIGH Clock Transition
$Q_0(\overline{Q}_0)$ = Previous Q($\overline{Q}$) before LOW-to-HIGH Transition of Clock

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.3 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150		150		150		MHz
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	CP_n to Q_n or $\overline{Q}_n$	1.5	7.0	1.5	8.0	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t_{PLH}	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	1.5	7.0	1.5	8.0	1.5	8.4	
t_S	Setup Time	2.5		2.5		4.0		ns
t_H	Hold Time	1.5		1.5		2.0		ns
t_W	Pulse Width CP	3.3		3.3		4.0		ns
t_W	Pulse Width and $\overline{C}_D$, $\overline{S}_D$	3.3		3.6		4.0		ns
t_{REC}	Recovery Time	2.5		3.0		4.5		ns
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 4)		1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Unit
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

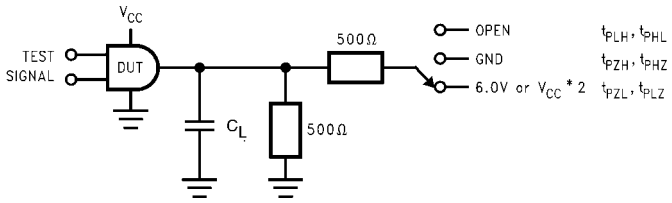
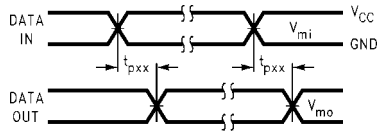
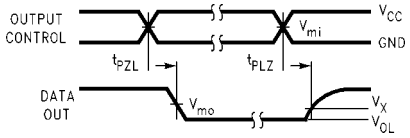


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

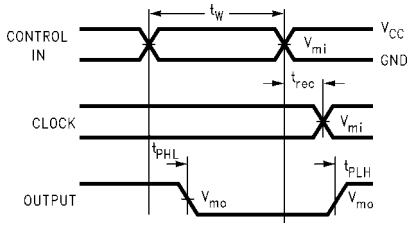
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



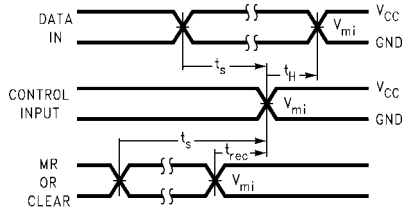
Waveform for Inverting and Non-Inverting Functions



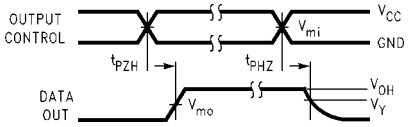
3-STATE Output Low Enable and Disable Times for Logic



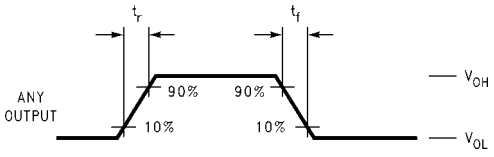
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

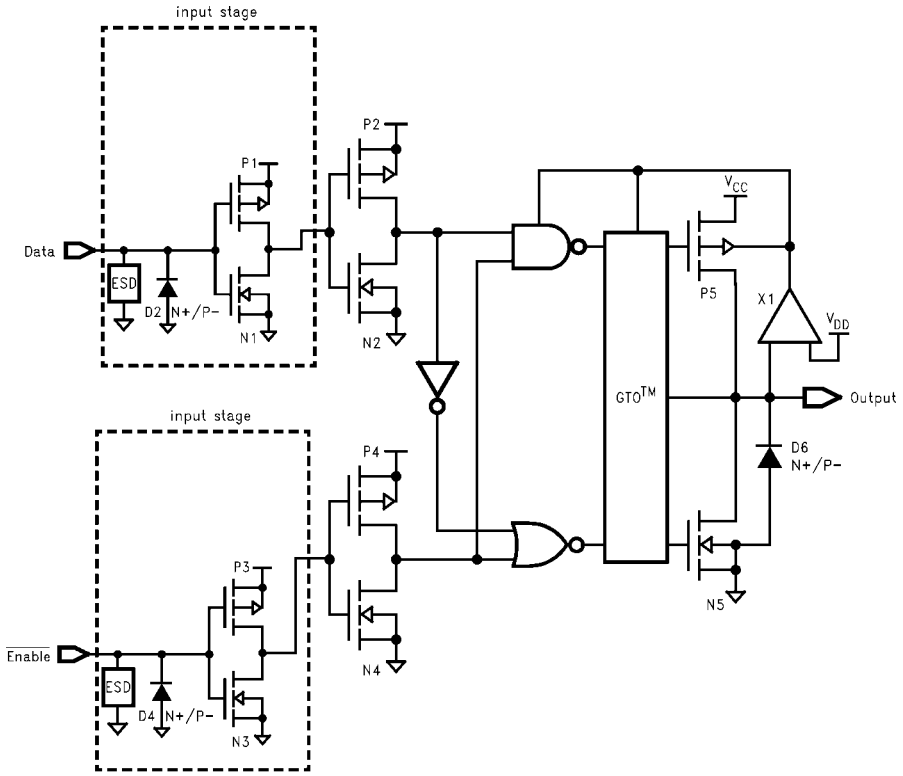


t_{rise} and t_{fall}

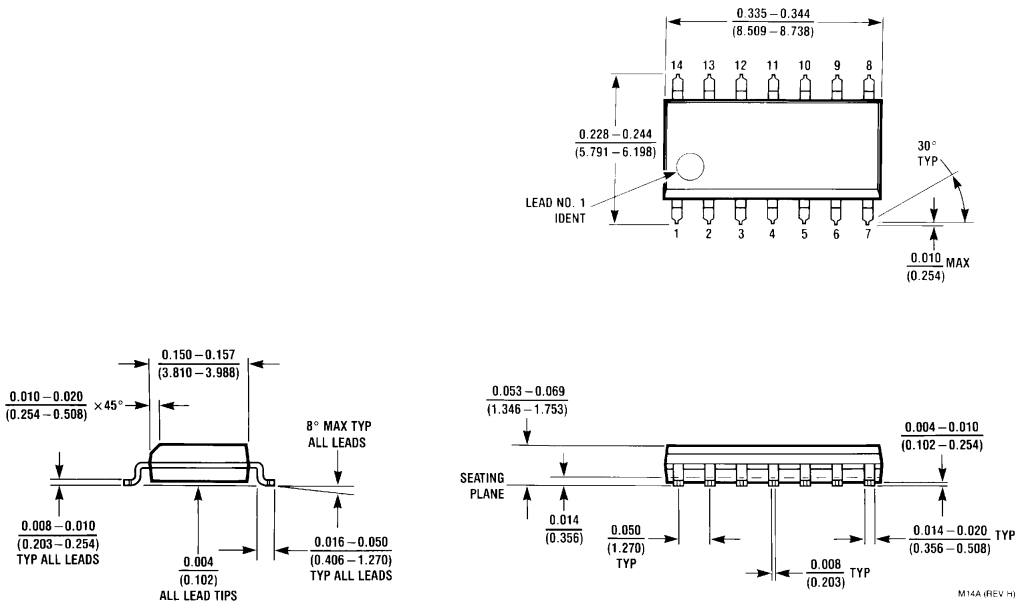
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

	V_{CC}		
Symbol	**3.3V ± 0.3V**	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

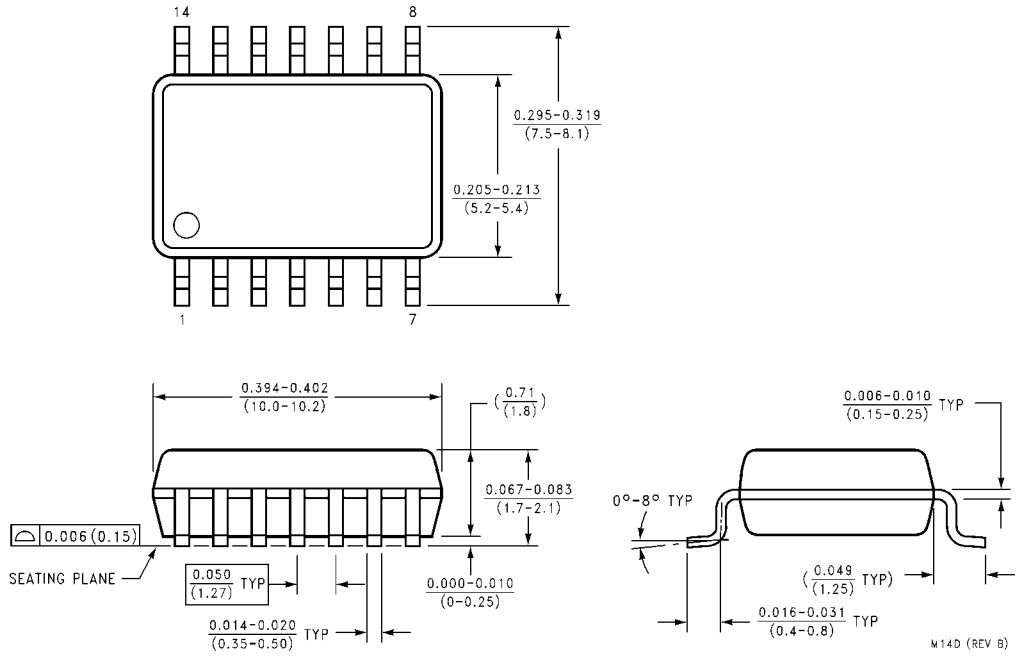
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

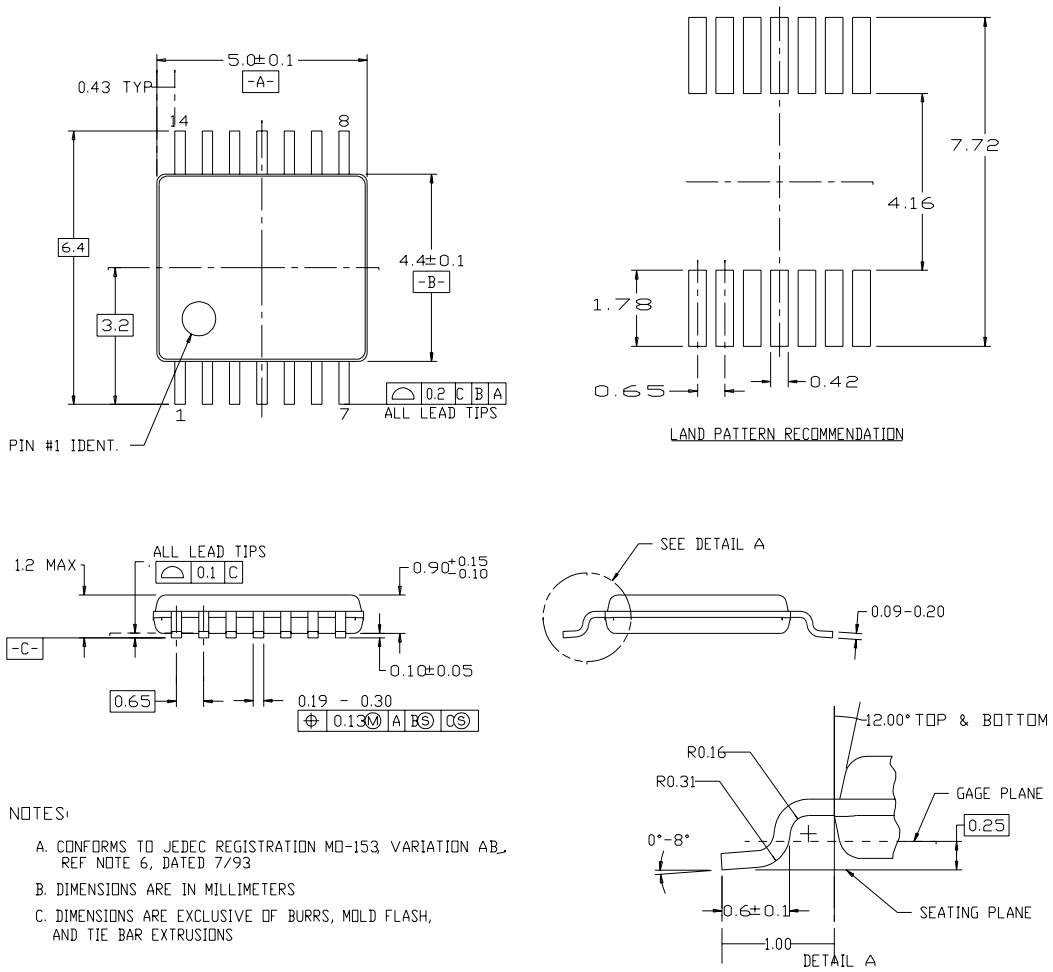


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

January 1996
Revised April 1999

74LCX821

Low Voltage 10-Bit D-Type Flip-Flop with 5V Tolerant Inputs and Outputs

General Description

The LCX821 consists of ten D-type Flip-Flops with 3-STATE outputs for bus organized system applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX821 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human Body Model > 2000V
  - Machine Model > 200V

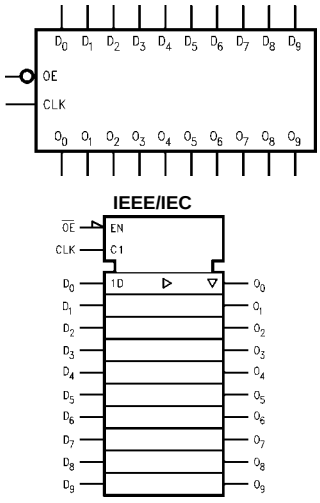
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

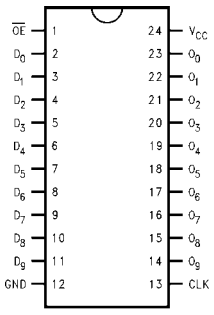
Order Number	Package Number	Package Description
74LCX821WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX821MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX821MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_9	Data Inputs
CLK	Clock Input
$\overline{OE}$	Output Enable Input
O_0–O_9	3-STATE Latch Outputs

Function Table

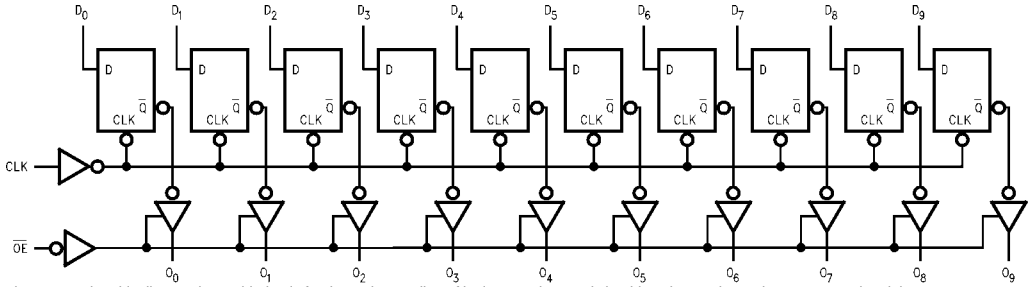
Inputs			Internal	Outputs	Function
$\overline{OE}$	CLK	D	Q	O_n	
H	H	L	NC	Z	Hold
H	H	H	NC	Z	Hold
H	↗	L	L	Z	Load
H	↗	H	H	Z	Load
L	↗	L	L	L	Data Available
L	↗	H	H	H	Data Available
L	H	L	NC	NC	No Change in Data
L	H	H	NC	NC	No Change in Data

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impendance
↗ = LOW-to-HIGH Transition
NC = No Change

Functional Description

The LCX821 consists of ten edge-triggered flip-flops with individual D-type inputs with 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The ten flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CLK) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the ten flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 – 3.6		±5.0	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150						MHz
t_{PHL}	Propagation Delay	1.5	7.0	1.5	7.5	1.5	8.4	ns
t_{PLH}	CLK to O_n	1.5	7.0	1.5	7.5	1.5	8.4	
t_{PZL}	Output Enable Time	1.5	7.5	1.5	8.0	1.5	9.8	ns
t_{PZH}		1.5	7.5	1.5	8.0	1.5	9.8	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 6)		1.0					
t_S	Setup Time, D_n to CLK	2.5		2.5		4.0		ns
t_H	Hold Time, D_n to CLK	1.5		1.5		2.0		ns
t_W	CLK Pulse Width	3.3		3.3		4.0		ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_O	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

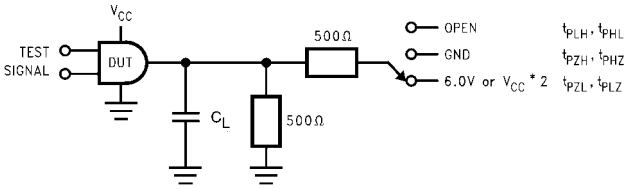
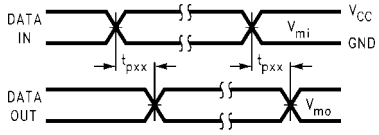
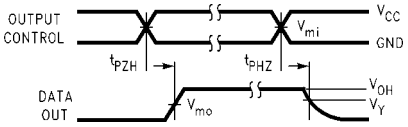


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

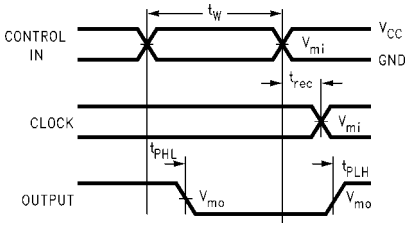
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



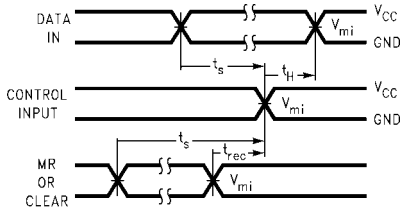
Waveform for Inverting and Non-Inverting Functions



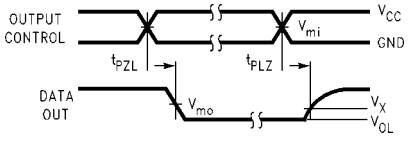
3-STATE Output High Enable and Disable Times for Logic



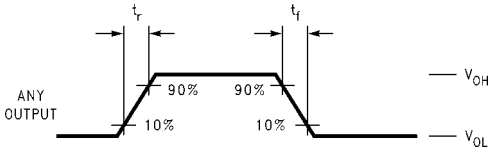
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

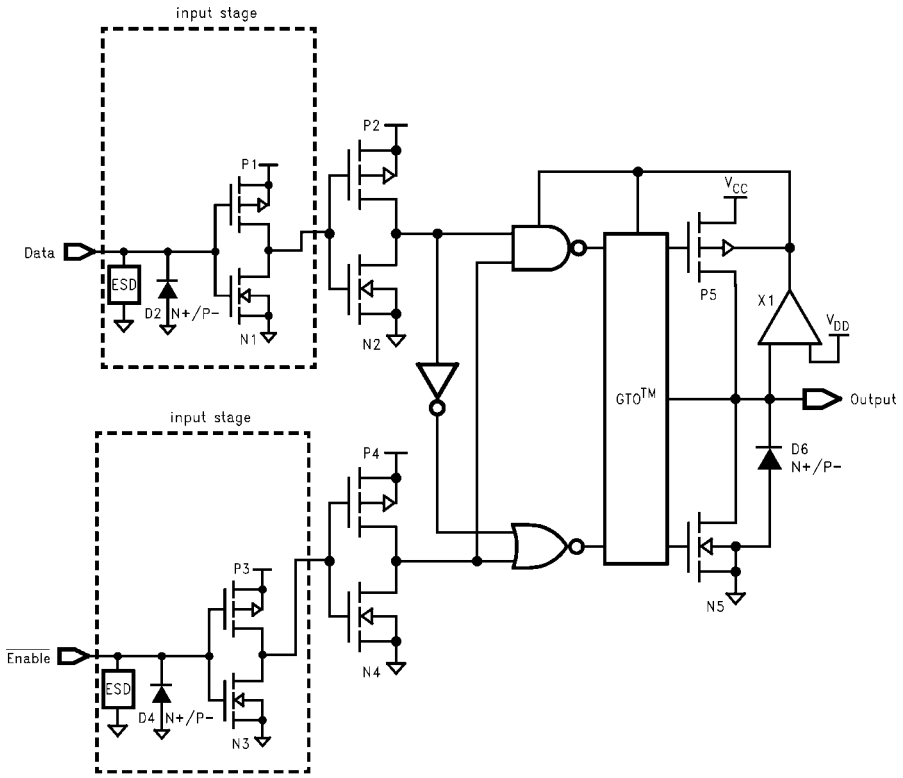


t_{rise} and t_{fall}

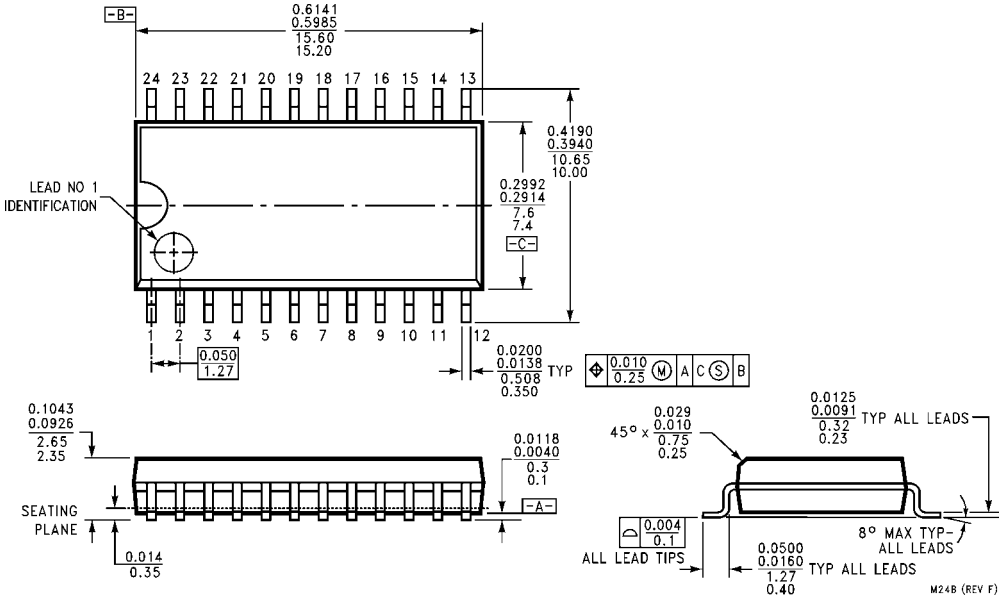
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

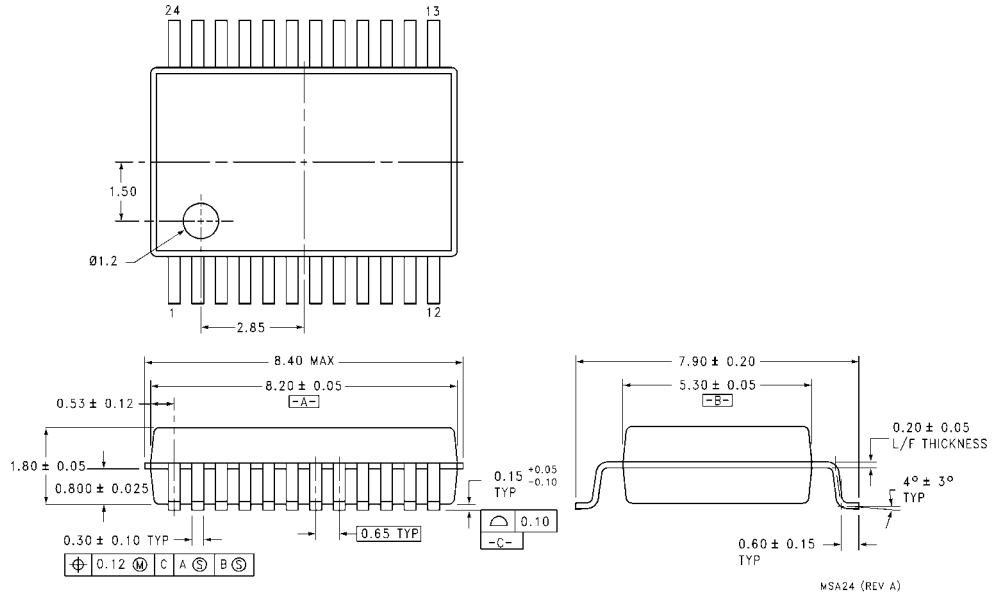
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

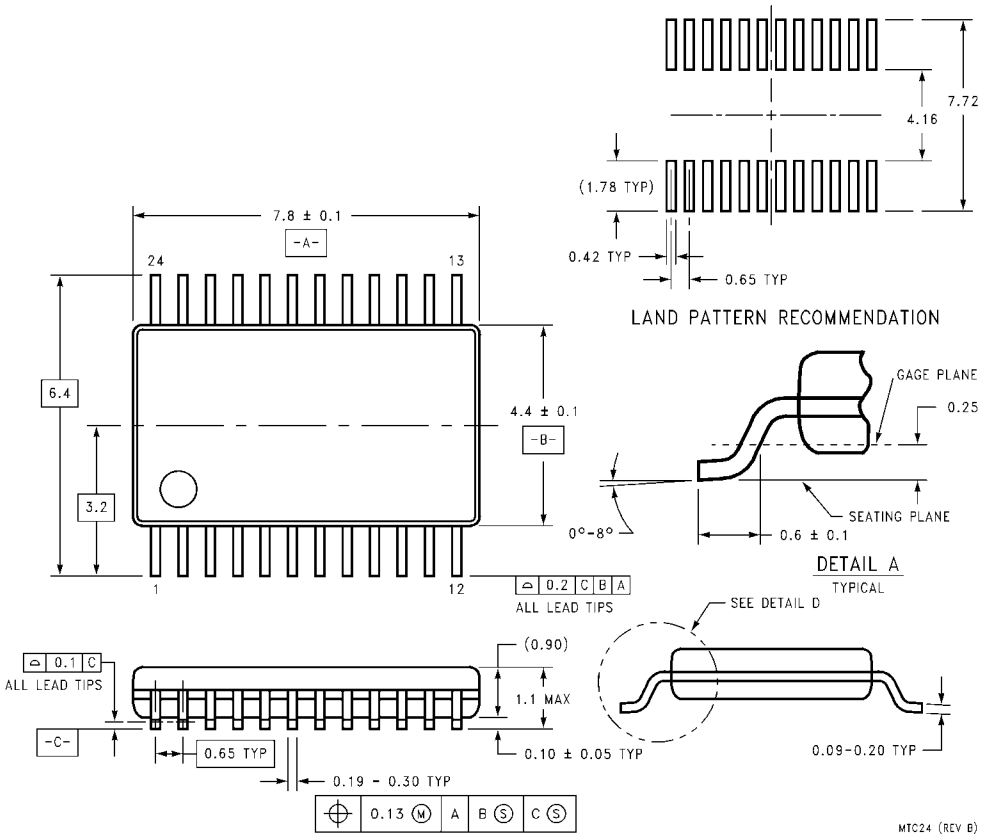


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1995
Revised April 1999

74LCX841

Low Voltage 10-Bit Transparent Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX841 consists of ten latches with 3-STATE outputs for bus organized system applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX841 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V – 3.6V V_{CC} specifications provided
- 8.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human Body Model > 2000V
  - Machine Model > 200V

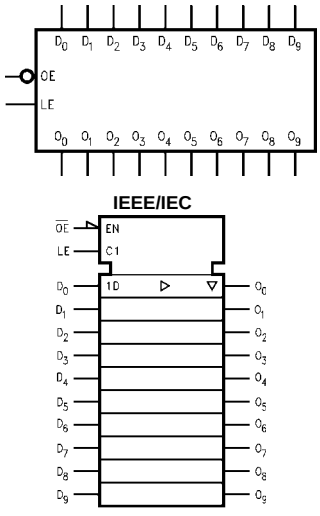
Note 1: To ensure the high-impedance state during power up or down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

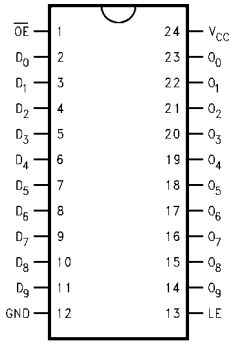
Order Number	Package Number	Package Description
74LCX841WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCX841MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX841MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_9	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_9	3-STATE Latch Outputs

Truth Table

Inputs			Internal	Output	Function
$\overline{OE}$	LE	D	Q	O	
X	X	X	X	Z	High Z
H	H	L	L	Z	High Z
H	H	H	H	Z	High Z
H	L	X	NC	Z	Latched
L	H	L	L	L	Transparent
L	H	H	H	H	Transparent
L	L	X	NC	NC	Latched

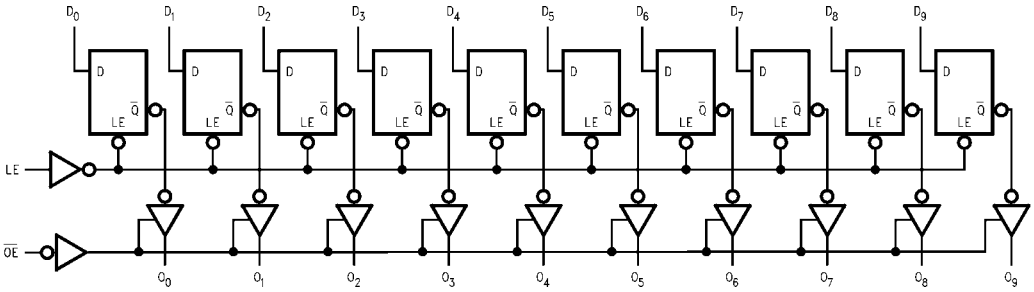
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impendance
NC = No Change

Functional Description

The LCX841 consists of ten D-type latches with 3-STATE outputs. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. This allows asynchronous operation, as the output transition follows the data in transition.

On the LE HIGH-to-LOW transition, the data that meets the setup and hold time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH the bus output is in the high impedance state.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V − 3.0V		±12	
		V_{CC} = 2.3V − 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V − 2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 − 2.7	1.7		V
			2.7 − 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 − 2.7		0.7	V
			2.7 − 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	2.3 − 3.6	V_{CC} − 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OH} = 100 μA	2.3 − 3.6		0.2	V
		I_{OH} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 − 3.6		±5.0	μA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 5.5V	2.3 − 3.6		±5.0	μA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	7.5	1.5	8.4	ns
t_{PLH}	D_n to O_n	1.5	7.0	1.5	7.5	1.5	8.4	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	7.5	1.5	8.4	ns
t_{PLH}	LE to O_n	1.5	7.0	1.5	7.5	1.5	8.4	
t_{PZL}	Output Enable Time	1.5	8.0	1.5	8.5	1.5	9.6	ns
t_{PZH}		1.5	8.0	1.5	8.5	1.5	9.6	
t_{PLZ}	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PHZ}		1.5	6.5	1.5	7.0	1.5	7.8	
t_{OSHL}	Output to Output Skew		1.0					ns
t_{OSLH}	(Note 6)		1.0					
t_S	Setup Time D_n to LE	2.5		2.5		4.0		ns
t_H	Hold Time D_n to LE	1.5		1.5		2.0		ns
t_W	LE Pulse Width	3.3		3.3		4.0		ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_O	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

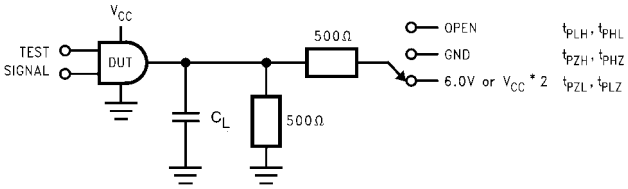
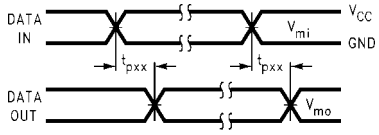
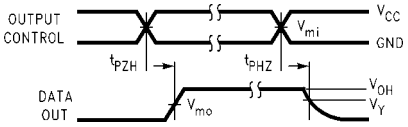


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

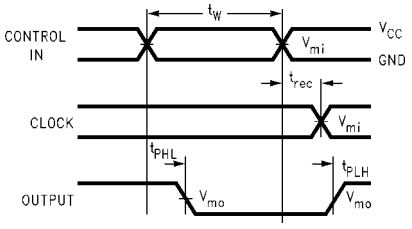
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



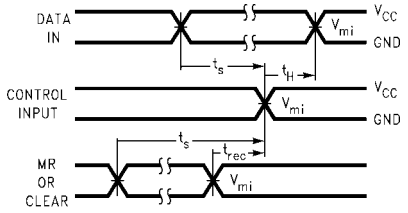
Waveform for Inverting and Non-Inverting Functions



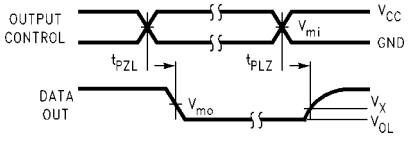
3-STATE Output High Enable and Disable Times for Logic



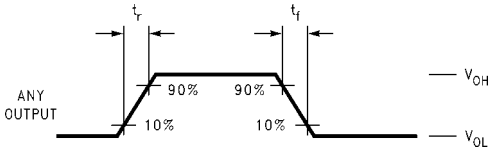
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

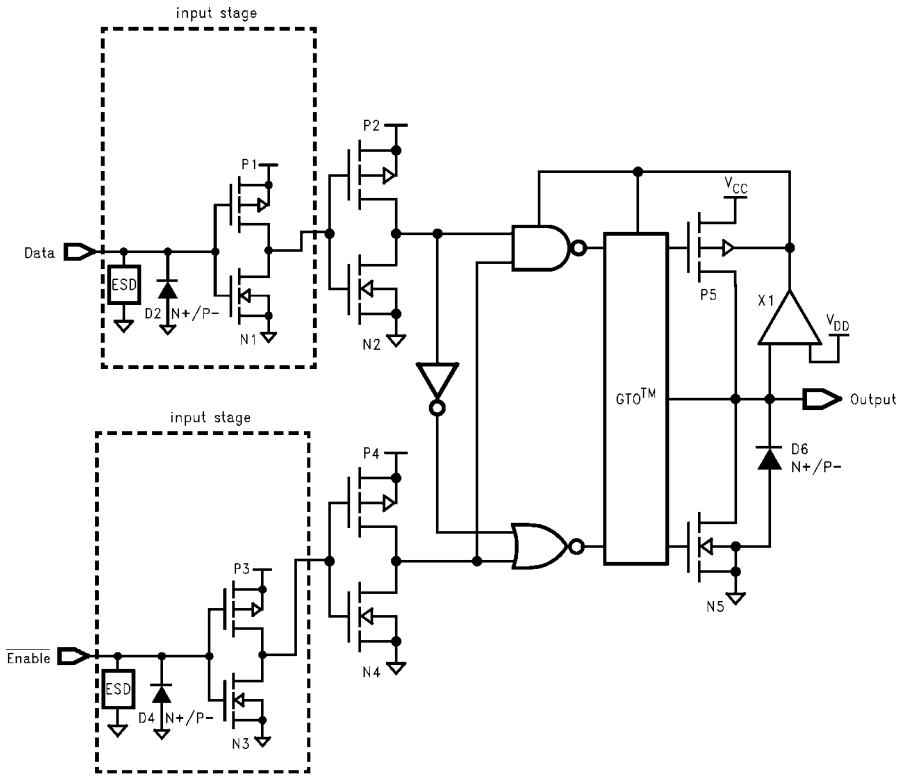


t_{rise} and t_{fall}

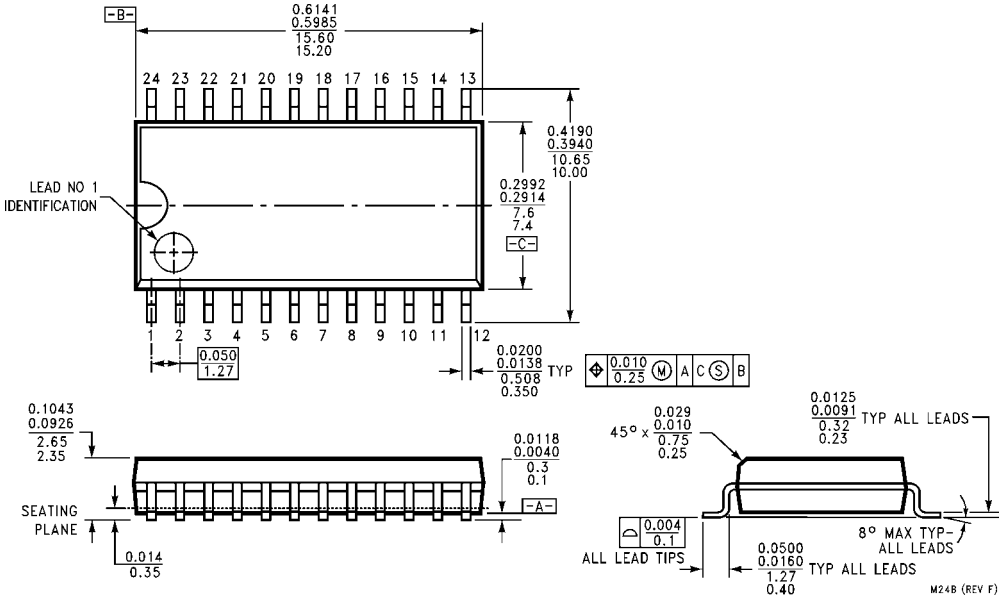
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

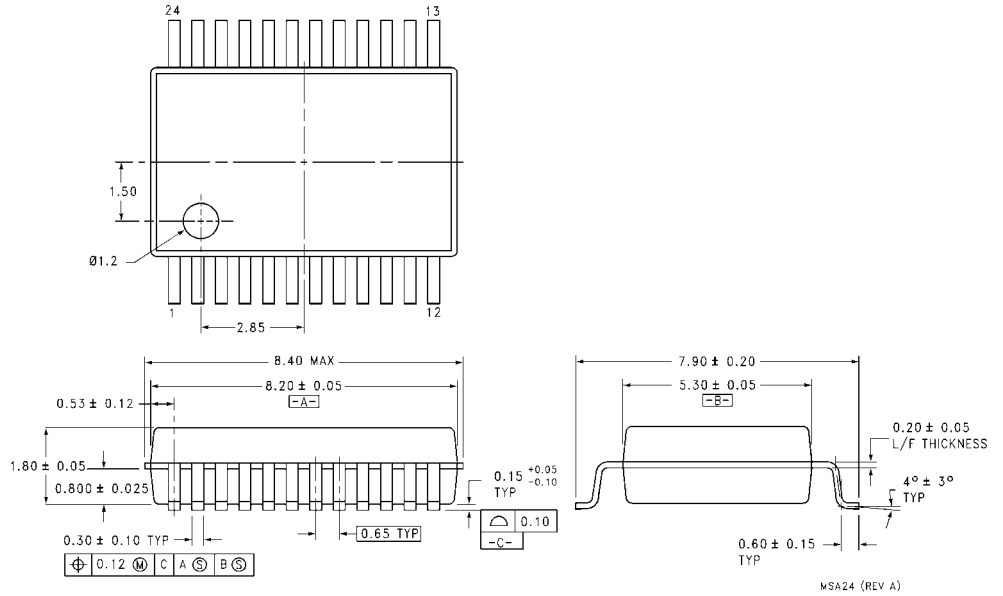
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

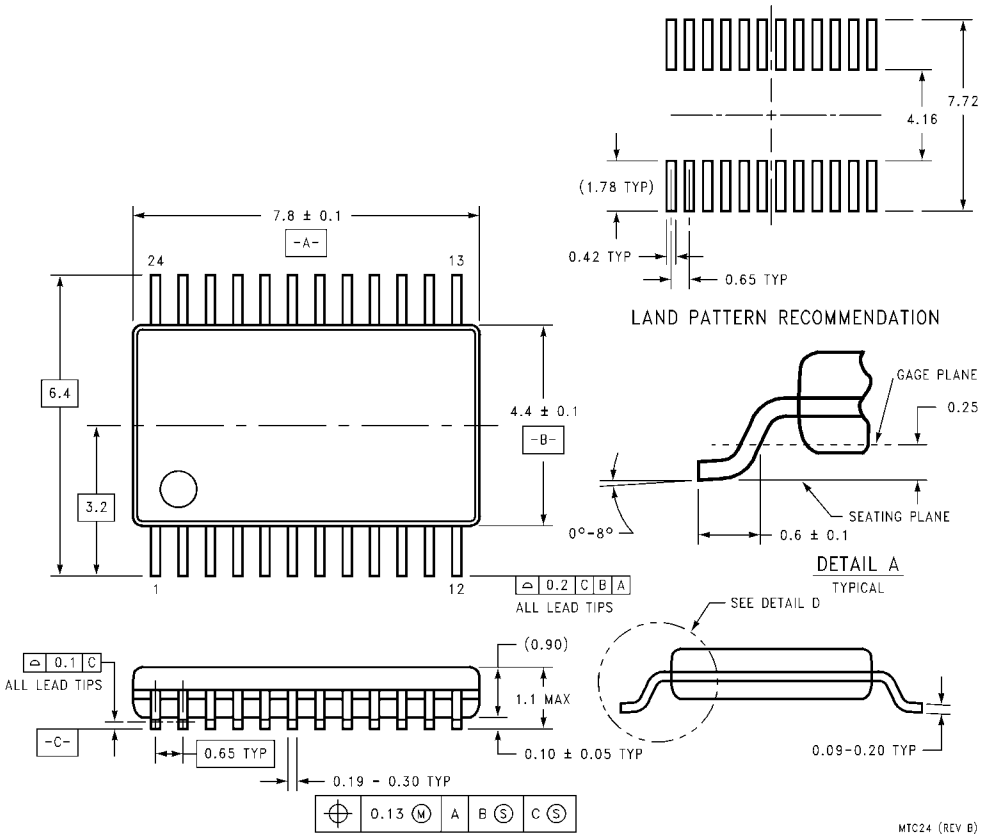


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1995
Revised March 1999

74LCX86
Low Voltage Quad 2-Input Exclusive-OR Gate with 5V Tolerant Inputs

General Description

The LCX86 contains four 2-input exclusive-OR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX86 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

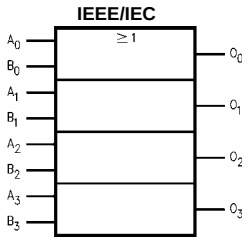
- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.5 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Machine model > 2000V
  - Human model > 200V

Ordering Code:

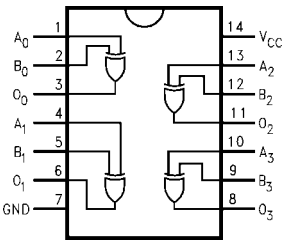
Order Number	Package Number	Package Description
74LCX86M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LCX86SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_3	Inputs
B_0–B_3	Inputs
O_0–O_3	Outputs

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to V_{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = –40°C to +85°C Min	T_A = –40°C to +85°C Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100µA	2.3 – 3.6	V_{CC} - 0.2		V
		I_{OH} = -8 mA	2.3	1.8		
		I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 – 3.6		0.2	V
		I_{OL} = 8mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3 – 3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.3 – 3.6		±10	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.3 – 3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	6.5	1.5	7.0	1.5	7.8	ns
t_{PLH}		1.5	6.5	1.5	7.0	1.5	7.8	
t_{OSHL}	Output to Output Skew (Note 4)		1.0					ns
t_{OSLH}			1.0					

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

AC Loading and Waveforms Generic for LCX Family

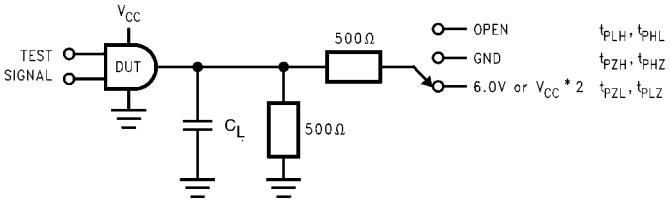
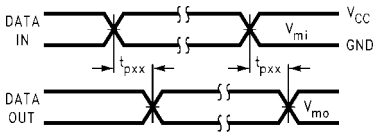
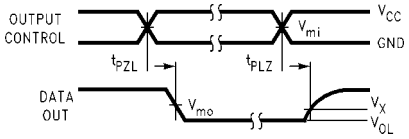


FIGURE 1. AC Test Circuit
(C_L includes probe and jig capacitance)

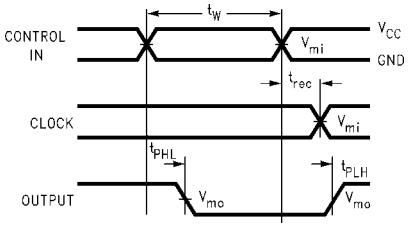
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



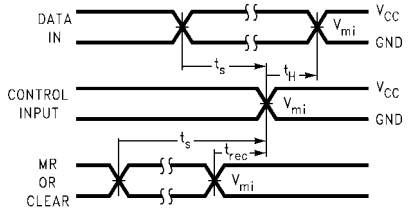
Waveform for Inverting and Non-Inverting Functions



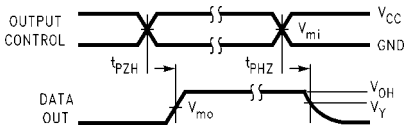
3-STATE Output Low Enable and Disable Times for Logic



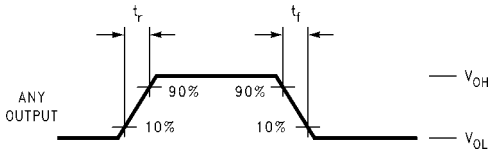
Propagation Delay, Pulse Width and t_{rec} Waveforms



Setup Time, Hold TIme and Recovery TIme for Logic



3-STATE Output High Enable and Disable TImes for Logic

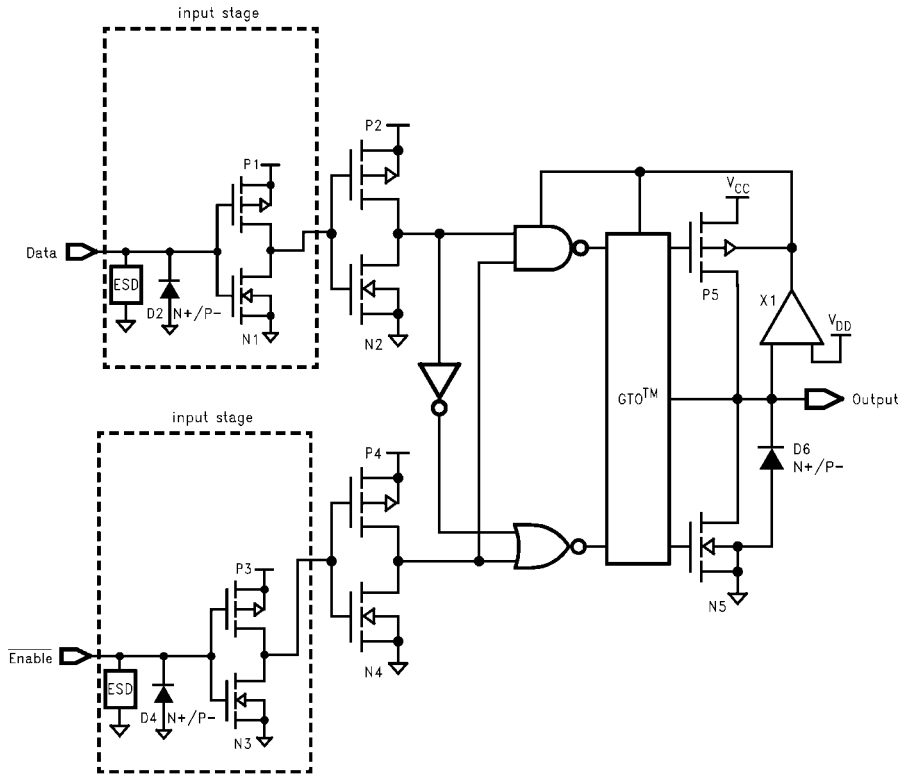


t_{rise} and t_{fall}

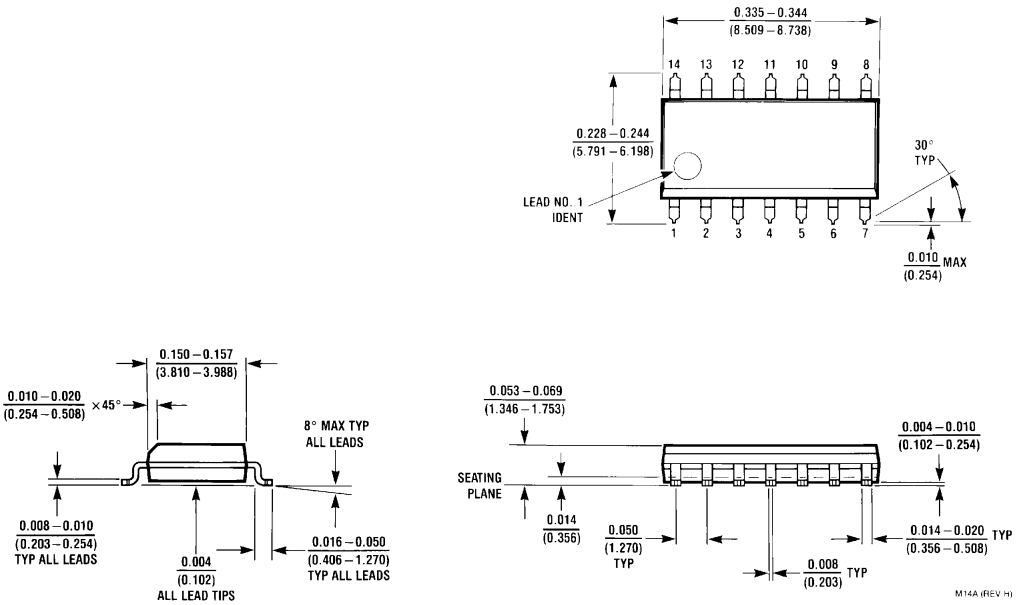
FIGURE 2. Waveforms
(Input Pulse Characteristics; f=1MHz, t_r=t_f=3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.7V**	**2.5V ± 0.2V**
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

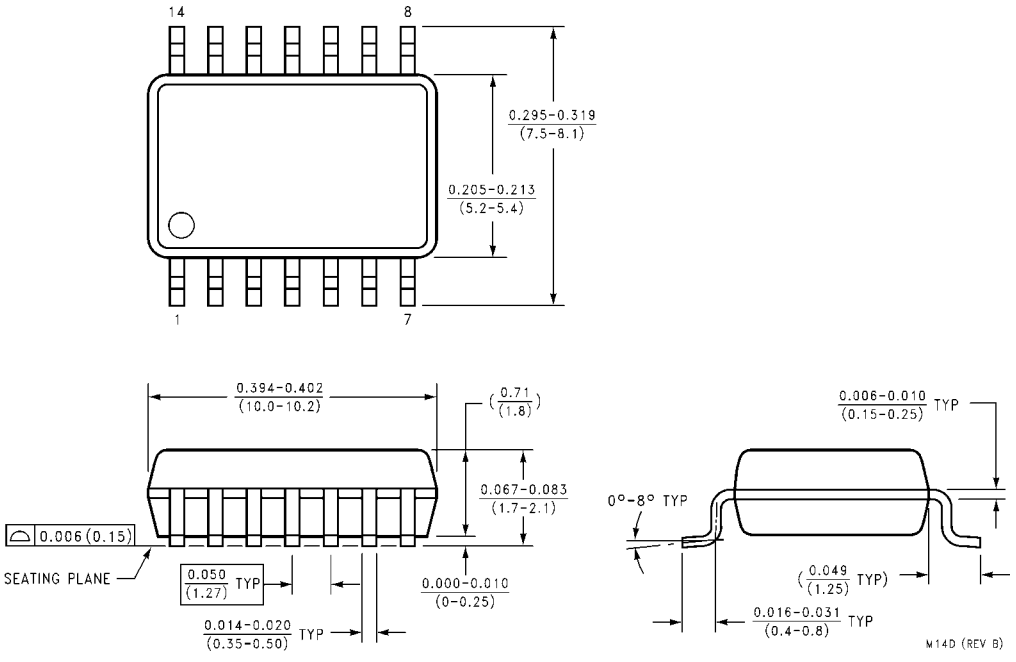
Schematic Diagram Generic for LCX Family



Physical Dimensions inches (millimeters) unless otherwise noted

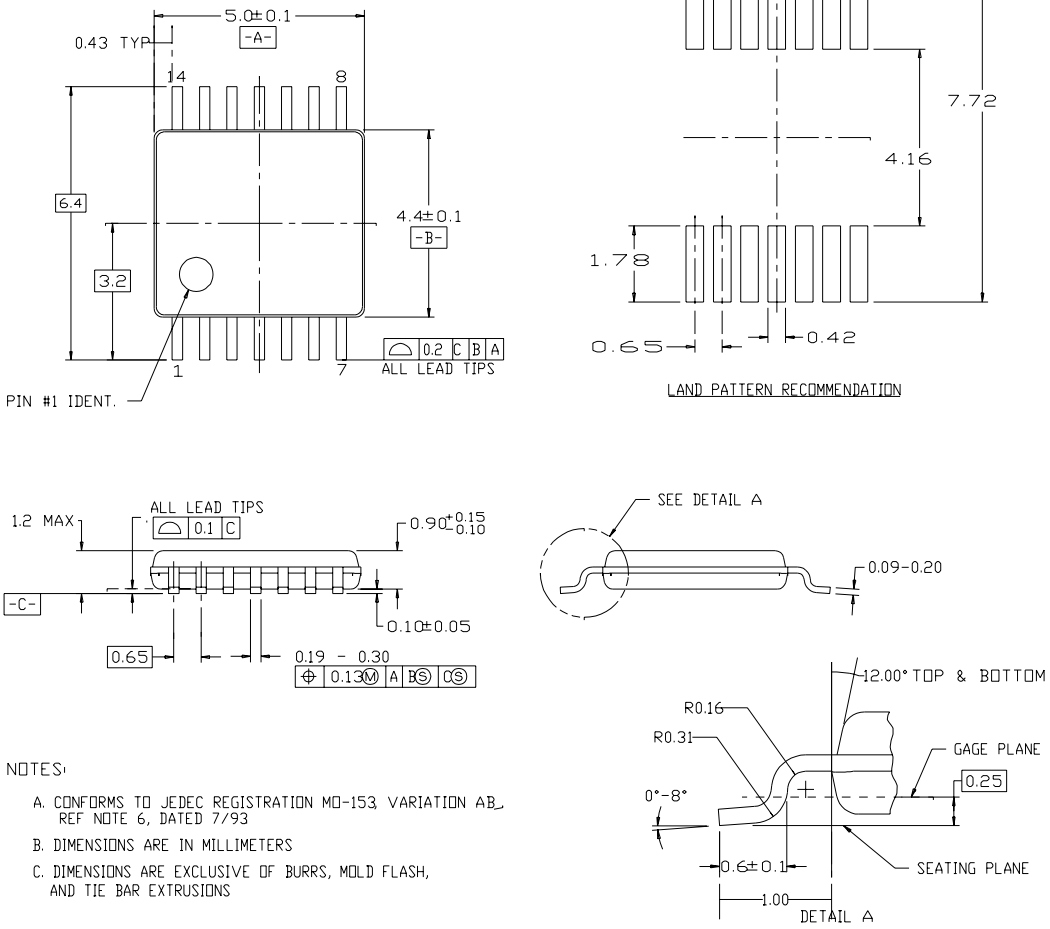


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

August 1998
Revised April 1999

74LCXP16245
Low Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs/Outputs and Pull-Down Resistors

General Description

The LCXP16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

In addition, A and B port datapath pins have built-in resistors to GND allowing the pins to float without any increase in I_{CC} current. This feature is intended to address modular and space constrained applications where additional space consumed by external resistors is not available.

The LCXP16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- I/O Pull-down resistors terminate inactive busses ensuring a stable bus state
- 5.5 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Pinout compatible with 74 series 16245
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

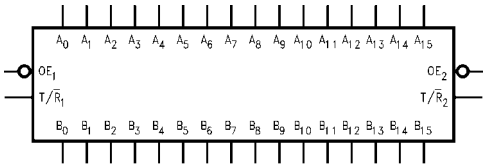
Note 1: To ensure the high-impedance state during power up or down $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCXP16245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCXP16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

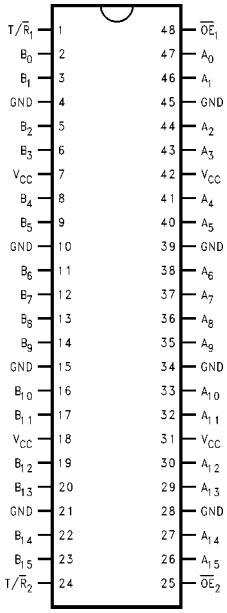
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input
T/$\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7 (Note 2)

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH Z State on A_8–A_{15}, B_8–B_{15} (Note 2)

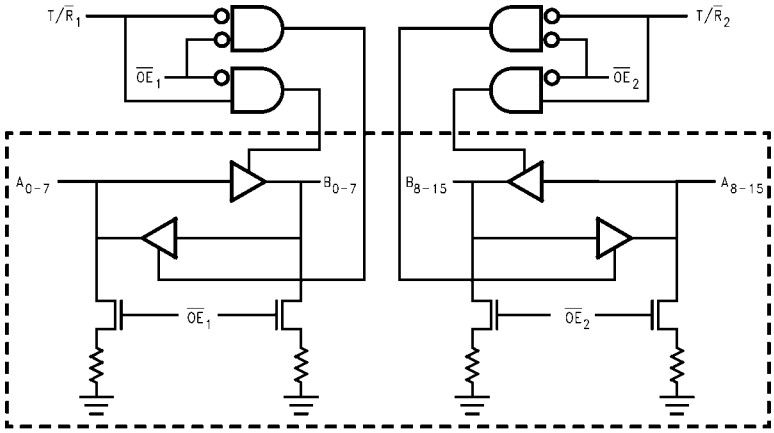
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Note 2: A and B port inputs are still active.

Functional Descriptions

The LCXP16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs. the device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state. The pulldown resistor (30KΩ normal) to GND is active only when the outputs are 3-STATED ($\overline{OE}$ = HIGH). When the outputs become active ($\overline{OE}$ = LOW) the resistor is removed from the circuit.

Logic Diagram



Absolute Maximum Ratings(Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 4)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V – 3.6V		±24	mA
		V_{CC} = 2.7V – 3.0V		±12	
		V_{CC} = 2.3V – 2.7V		±8	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −8 mA	2.3	1.8		
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 8 mA	2.3		0.6	
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 16 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA
$I_{OZ(L)}$	3-STATE I/O Leakage	V_I or V_O = 0.0V	2.3 – 3.6		±5.0	µA
$I_{OZ(H)}$	3-STATE I/O Leakage	V_I or V_O = 5.5V	2.3 – 3.6	50	500	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	µA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	µA

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$VCC = 2.5V \pm 0.2V$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 50$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.0	1.5	6.6	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	5.5	1.5	6.0	1.5	6.6	
t_{PZL}	Output Enable Time	1.5	7.0	1.5	8.0	1.5	9.1	ns
t_{PZH}		1.5	7.0	1.5	8.0	1.5	9.1	
t_{PLZ}	Output Disable Time	1.5	7.0	1.5	7.5	1.5	8.4	ns
t_{PHZ}		1.5	7.0	1.5	7.5	1.5	8.4	
t_{OSHL}	Output to Output Skew (Note 6)		1.0					ns
t_{OSLH}			1.0					

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.8	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

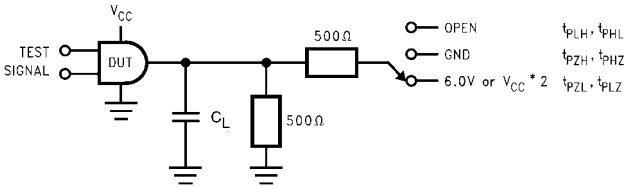
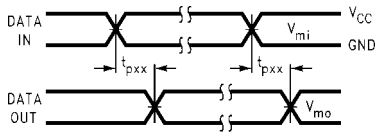
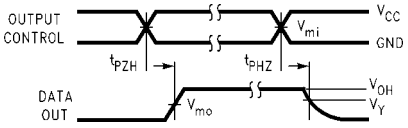


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

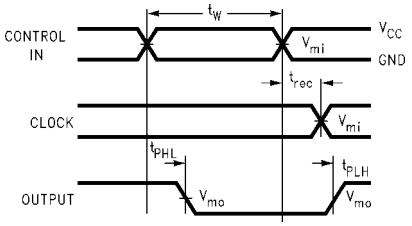
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



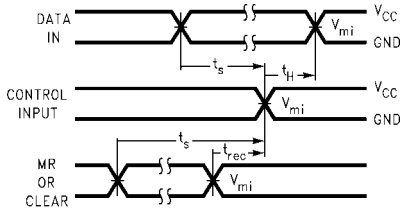
Waveform for Inverting and Non-Inverting Functions



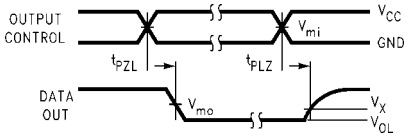
3-STATE Output High Enable and Disable Times for Logic



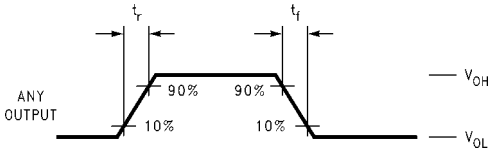
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

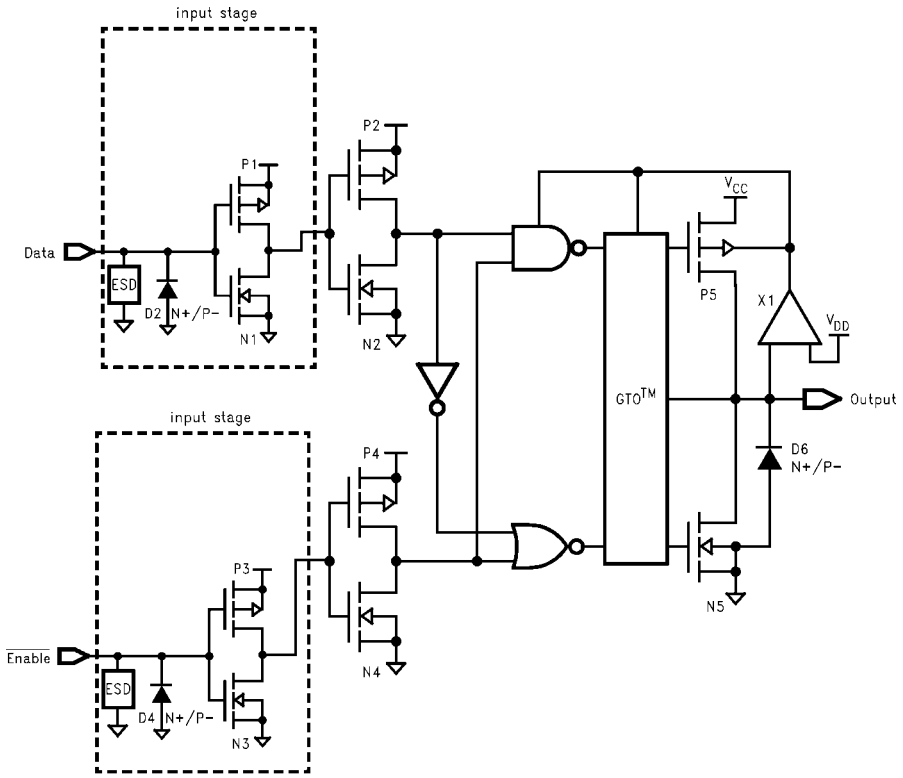


t_{rise} and t_{fall}

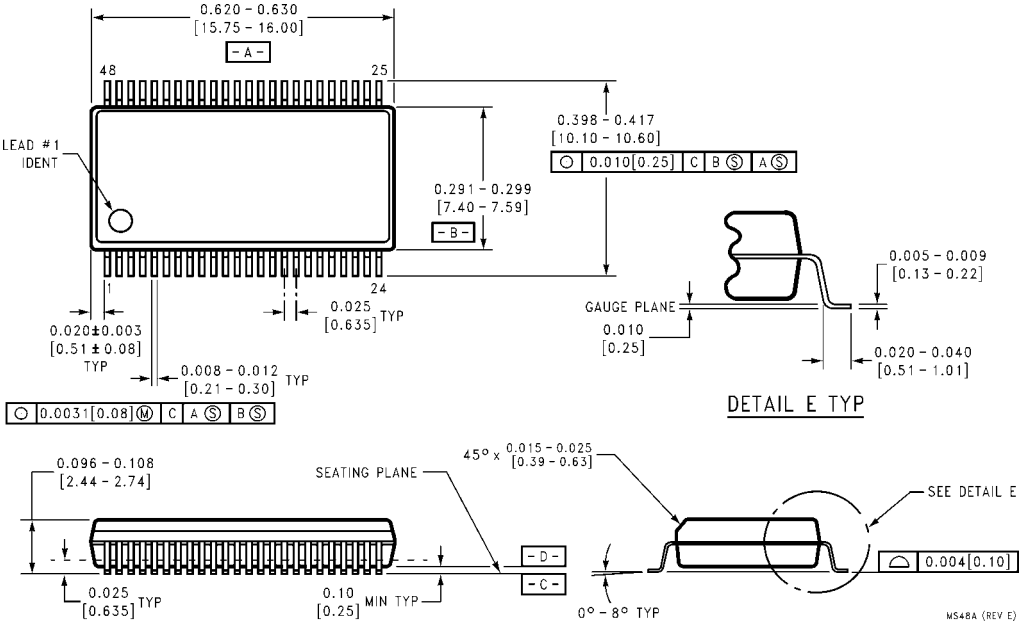
FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family

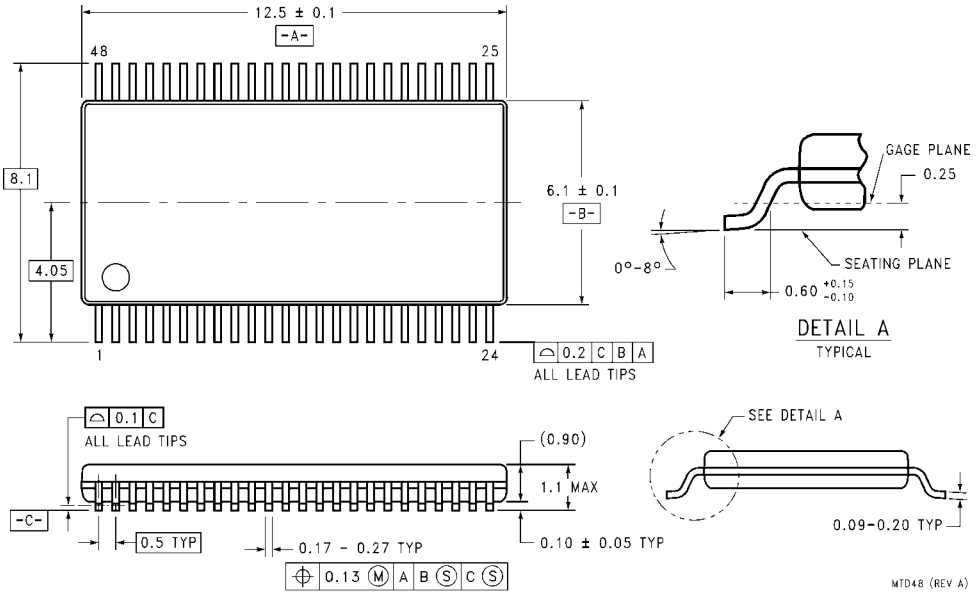


Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC, MO-153, 6.1mm Wide
Package Number MTD48

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

August 1998
Revised April 1999

74LCXR162245
Low Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs/Outputs and 26Ω Series Resistors in the Outputs

General Description

The LCXR162245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

In addition, all A and B outputs include equivalent 26Ω (nominal) series resistors to reduce overshoot and undershoot and are designed to sink/source up to 12 mA at V_{CC} = 3.0V.

The LCXR162245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- A and B side outputs have equivalent 26Ω series resistors
- 5.3 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Flow through pinout
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

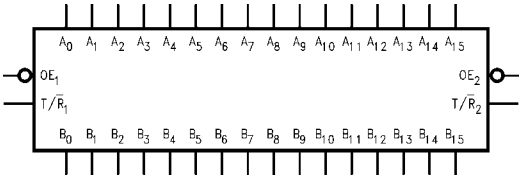
Note 1: To ensure the high-impedance state during power up or down $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCXR162245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCXR162245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "x" to the ordering code.

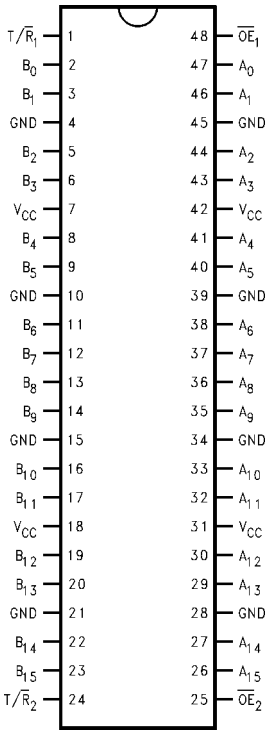
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input
T/$\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

Connection Diagram



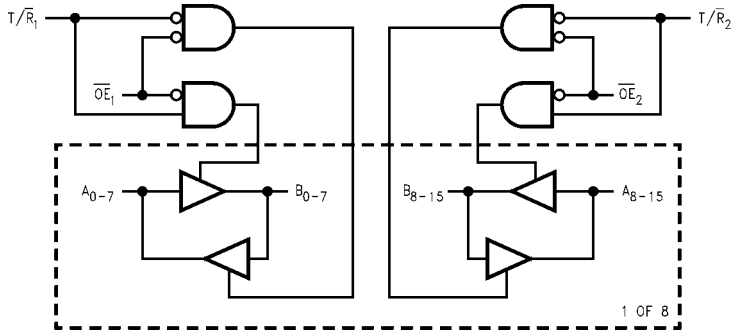
Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7 (Note 2)

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH Z State on A_8–A_{15}, B_8–B_{15} (Note 2)

Note 2: A and B port inputs are still active

Logic Diagram



Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0 −0.5 to V_{CC} + 0.5	Output in 3-STATE Output in HIGH or LOW State (Note 4)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50 +50	V_O < GND V_O > V_{CC}	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		3-STATE	0	5.5	
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±12	mA
		V_{CC} = 2.7V − 3.0V		±8	
		V_{CC} = 2.3V − 2.7V		±4	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused pins (Inputs or I/O's) must be held HIGH or LOW. They may not Float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = −40°C to +85°C		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −4 mA	2.3	1.8		
		I_{OH} = −4 mA	2.7	2.2		
		I_{OH} = −6 mA	3.0	2.4		
		I_{OH} = −8 mA	2.7	2.0		
		I_{OH} = −12 mA	3.0	2.0		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 3.6		0.2	V
		I_{OL} = 4 mA	2.3		0.6	
		I_{OL} = 4 mA	2.7		0.4	
		I_{OL} = 6 mA	3.0		0.55	
		I_{OL} = 8 mA	2.7		0.6	
		I_{OL} = 12 mA	3.0		0.8	
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.3 – 3.6		±5.0	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units
				Min	Max	
I_{OZ}	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 – 3.6		±5.0	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power-Off Leakage Current	V_I or $V_O = 5.5V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 6)	2.3 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2$		
		$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.3	1.5	6.0	1.5	6.4	ns
t_{PLH}	A_n to B_n or B_n to A_n	1.5	5.3	1.5	6.0	1.5	6.4	
t_{PZL}	Output Enable Time	1.5	7.3	1.5	8.0	1.5	9.5	ns
t_{PZH}		1.5	7.3	1.5	8.0	1.5	9.5	
t_{PLZ}	Output Disable Time	1.5	6.4	1.5	6.9	1.5	7.7	ns
t_{PHZ}		1.5	6.4	1.5	6.9	1.5	7.7	
t_{OSHL}	Output to Output Skew (Note 7)		1.0					ns
t_{OSLH}			1.0					

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.35	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	0.25	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	–0.35	V
		$C_L = 30$ pF, $V_{IH} = 2.5V$, $V_{IL} = 0V$	2.5	–0.25	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

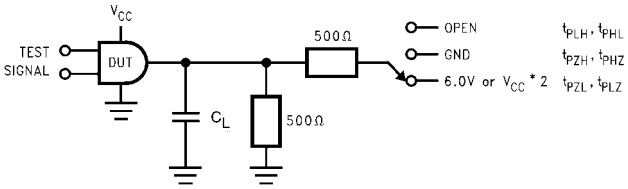
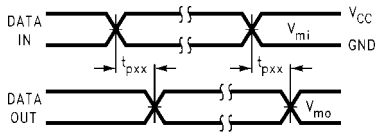
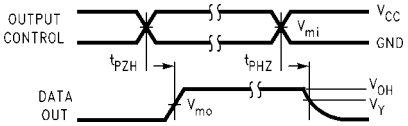


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

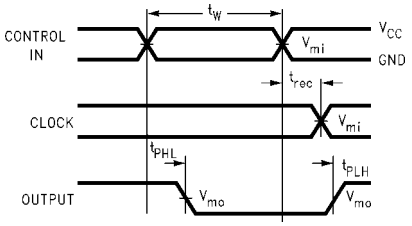
Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND



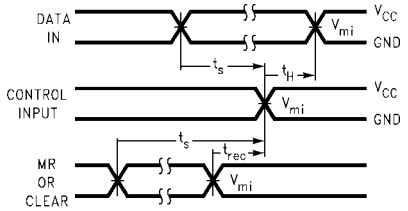
Waveform for Inverting and Non-Inverting Functions



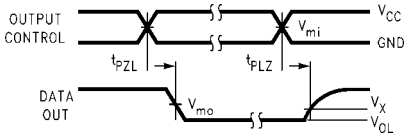
3-STATE Output High Enable and Disable Times for Logic



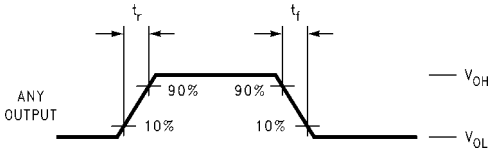
Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

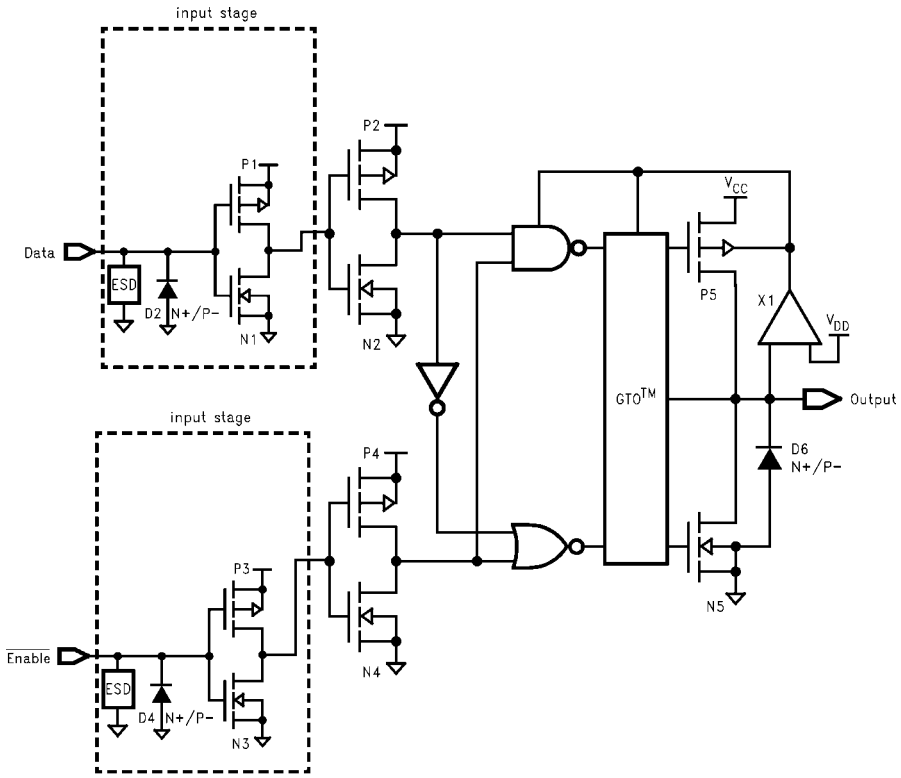


t_{rise} and t_{fall}

FIGURE 2. Waveforms
(Input Characteristics; f =1MHz, t_R = t_F = 3ns)

Symbol	V_{CC}		
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V_{CC}/2
V_{mo}	1.5V	1.5V	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.3V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.3V	V_{OH} − 0.15V

Schematic Diagram Generic for LCX Family



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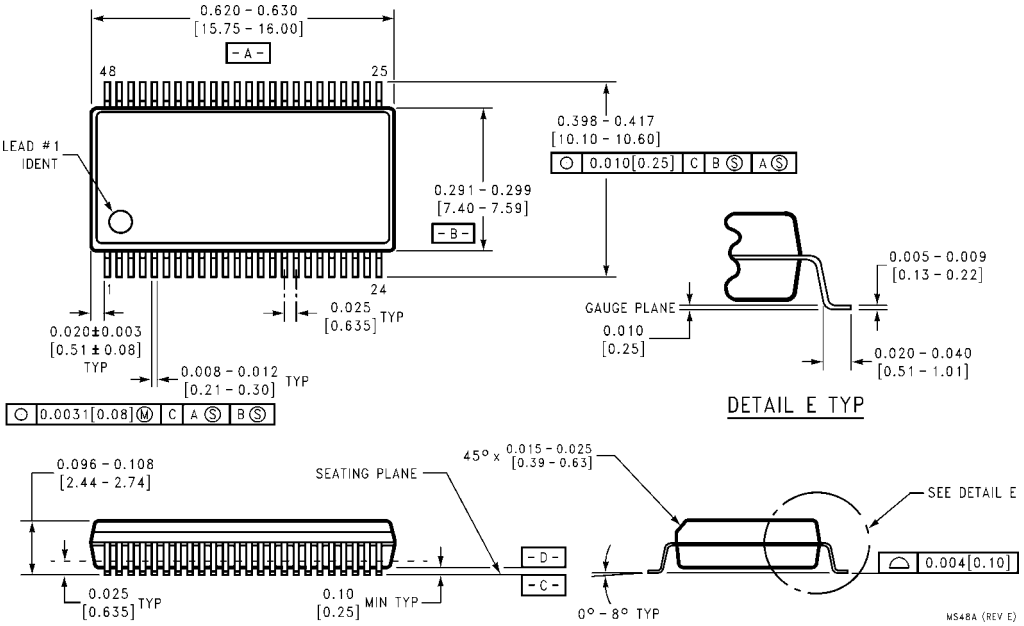
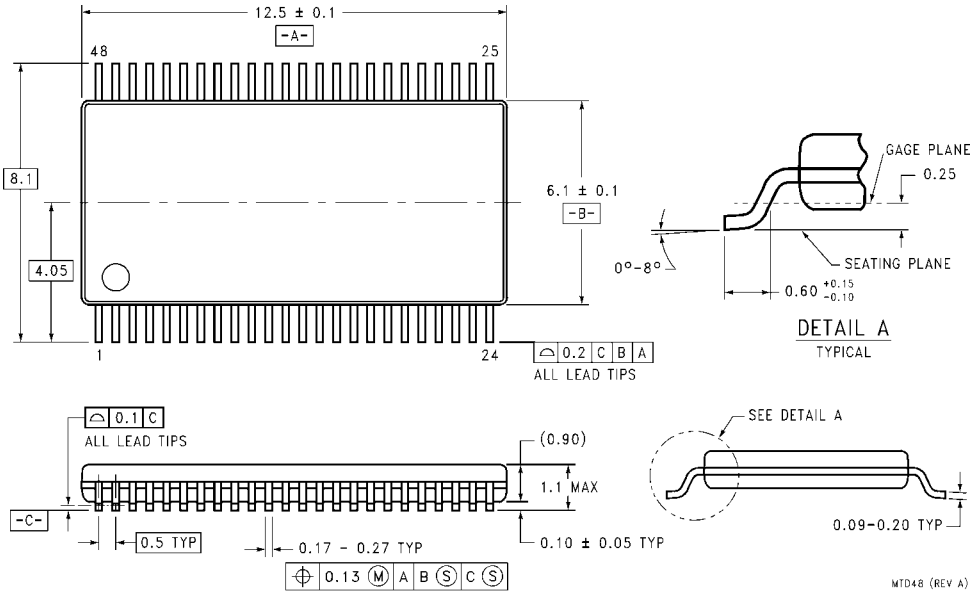


48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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November 1997

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74LVQ00
Low Voltage Quad 2-Input NAND Gate

General Description

The LVQ00 contains four 2-input NAND gates.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

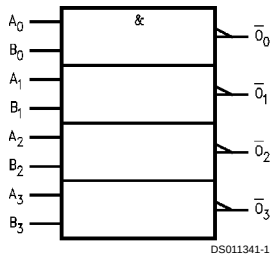
Ordering Code: See

Order Number	Package Number	Package Description
74LVQ00SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
74LVQ00SJ	M14D	14-Lead Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

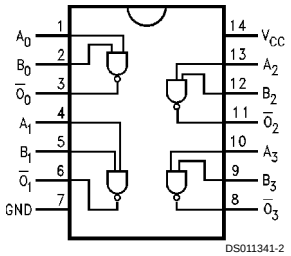
IEEE/IEC



DS011341-1

Connection Diagram

Pin Assignment for for SOIC JEDEC and EIAJ



DS011341-2

Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	
LVQ	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74LVQ	−40˚C to +85˚C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C		T_A = −40˚C to +85˚C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} I_{OH} = −12 mA (Note 3)
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} I_{OL} = 12 mA (Note 3)
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.6	1.0		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−1.0		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.5	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.5	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

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AC Electrical Characteristics

See for Test Methodology

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	2.0	8.4	13.4	2.0	14.0	ns
		3.3 ± 0.3	2.0	7.0	9.5	2.0	10.0	
t_{PHL}	Propagation Delay	2.7	1.5	6.6	11.3	1.0	12.0	ns
		3.3 ± 0.3	1.5	5.5	8.0	1.0	8.5	
t_{OSHL},	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	(Note 9)	3.3 ± 0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	22	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Book Extract End

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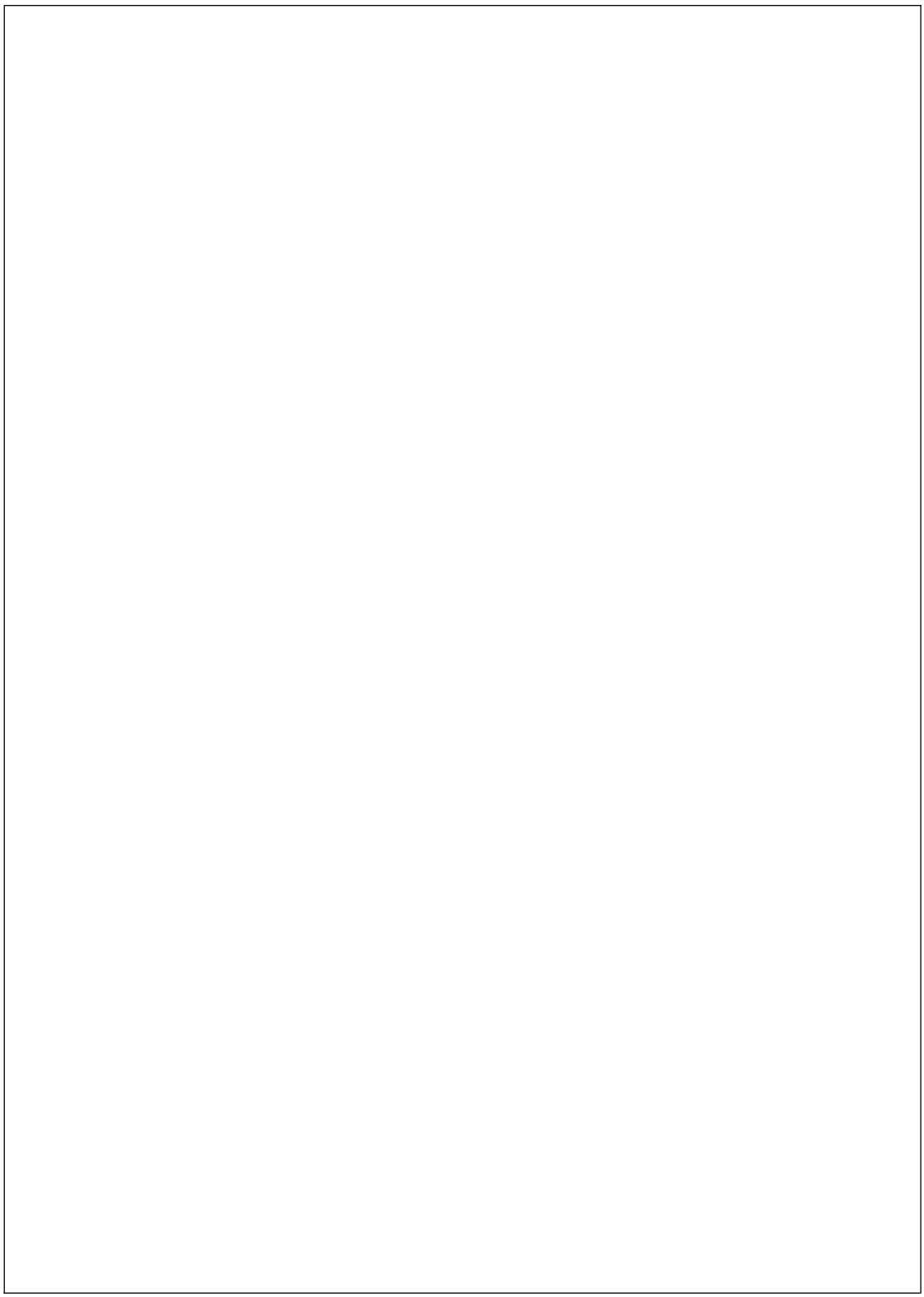
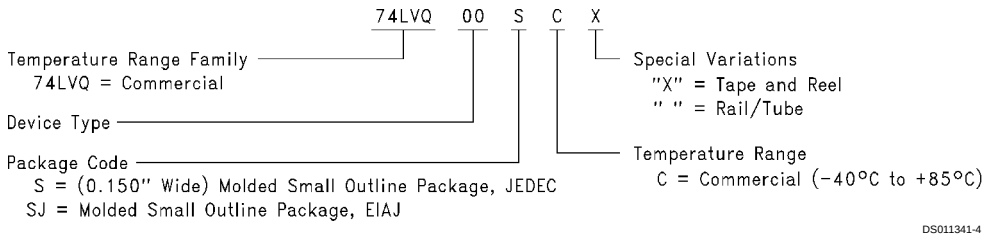


PrintDate=1997/11/10 PrintTime=09:36:42 23554 ds011341 Rev. No. 4 cmserv **Proof**

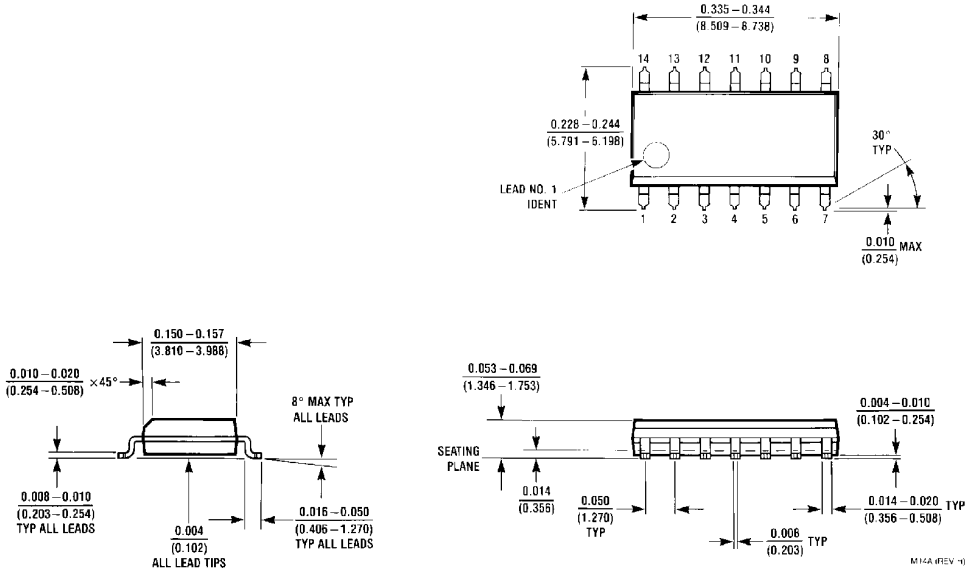
Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



DS011341-4

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit (S)
Package Number M14A

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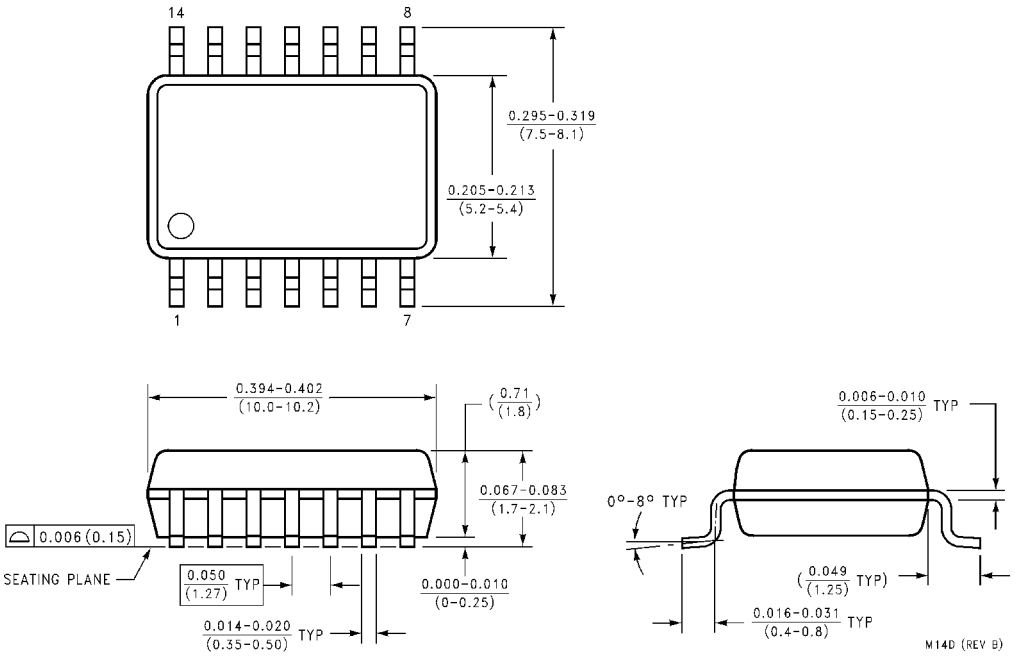
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Small Outline Package, EIAJ (SJ)
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ02
Low Voltage Quad 2-Input NOR Gate

General Description

The LVQ02 contains four 2-input NOR gates.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

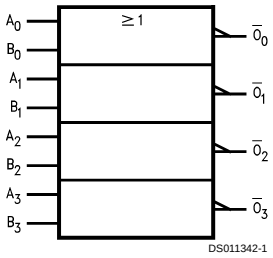
Ordering Code:

Order Number	Package Number	Package Description
74LVQ02SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
74LVQ02SJ	M14D	14-Lead Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

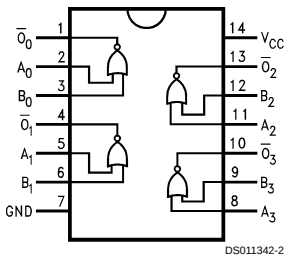
IEEE/IEC



DS011342-1

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011342-2

Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	
LVQ	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74LVQ	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.6	1.0		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.7	−1.0		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.7	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

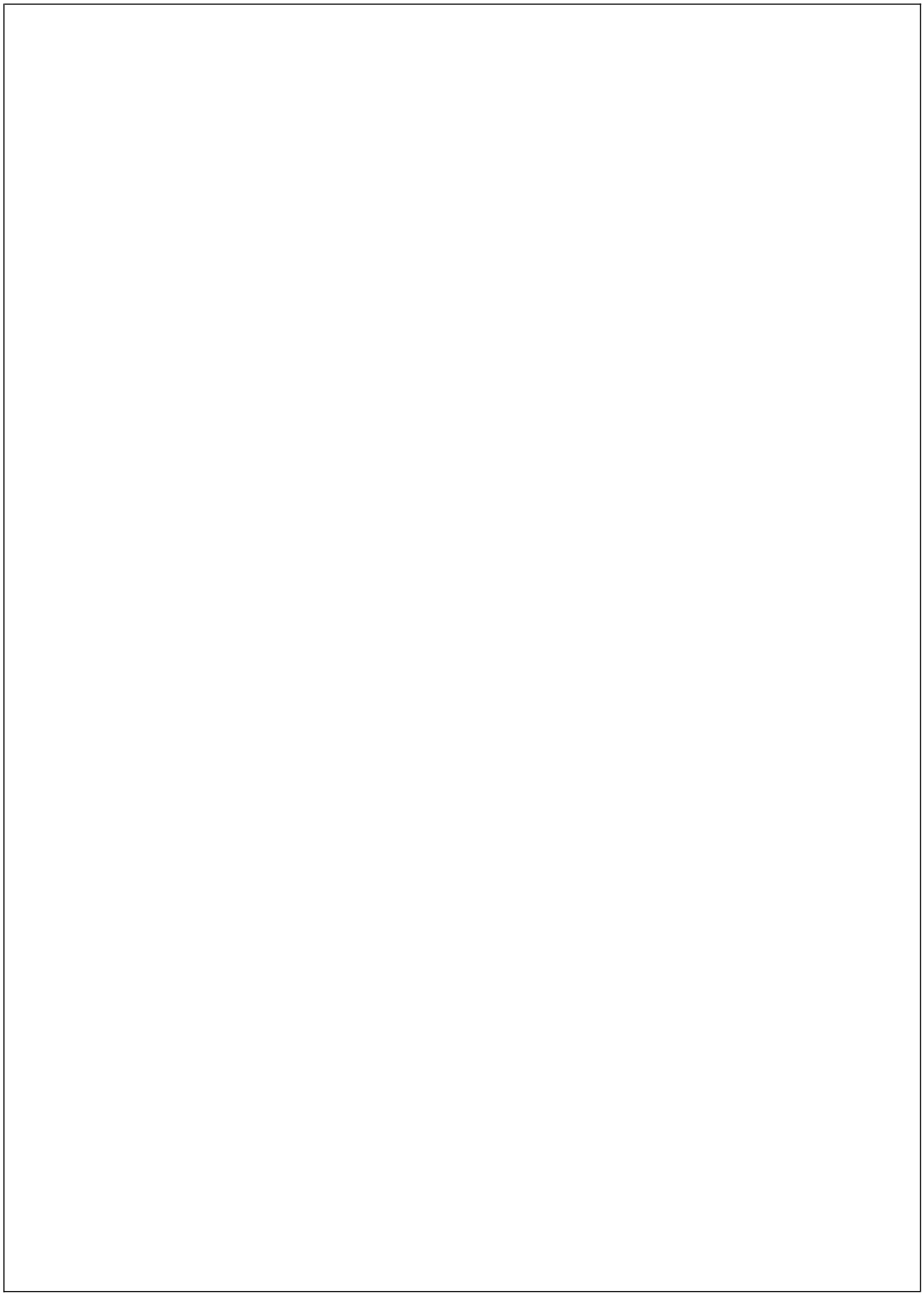
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	6.0	10.6	1.0	12.0	
		3.3 ±0.3	1.5	5.0	7.5	1.0	8.0	ns
t_{PHL}	Propagation Delay	2.7	1.5	6.0	10.6	1.0	12.0	
		3.3 ±0.3	1.5	5.0	7.5	1.0	8.0	ns
$t_{OSHL,}$	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

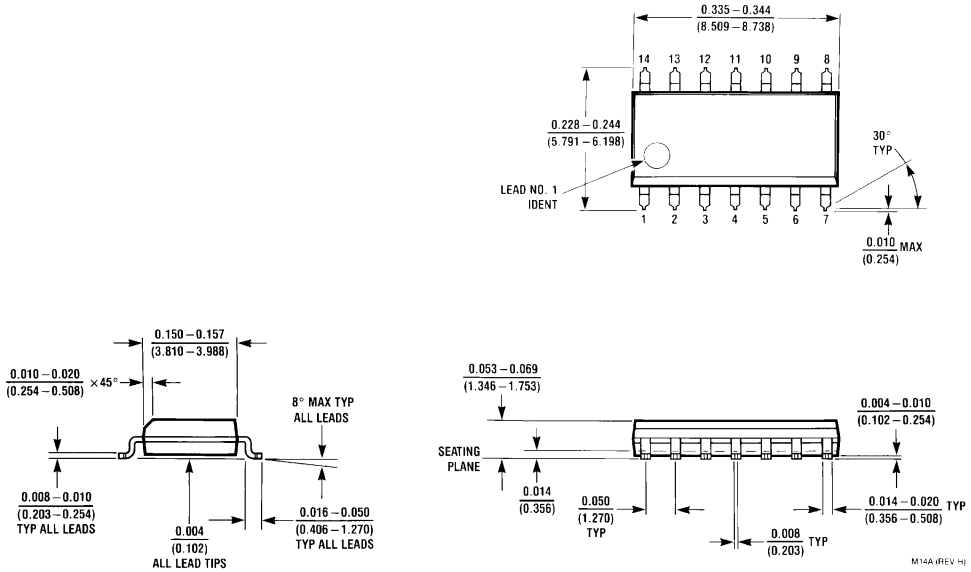
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	20	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

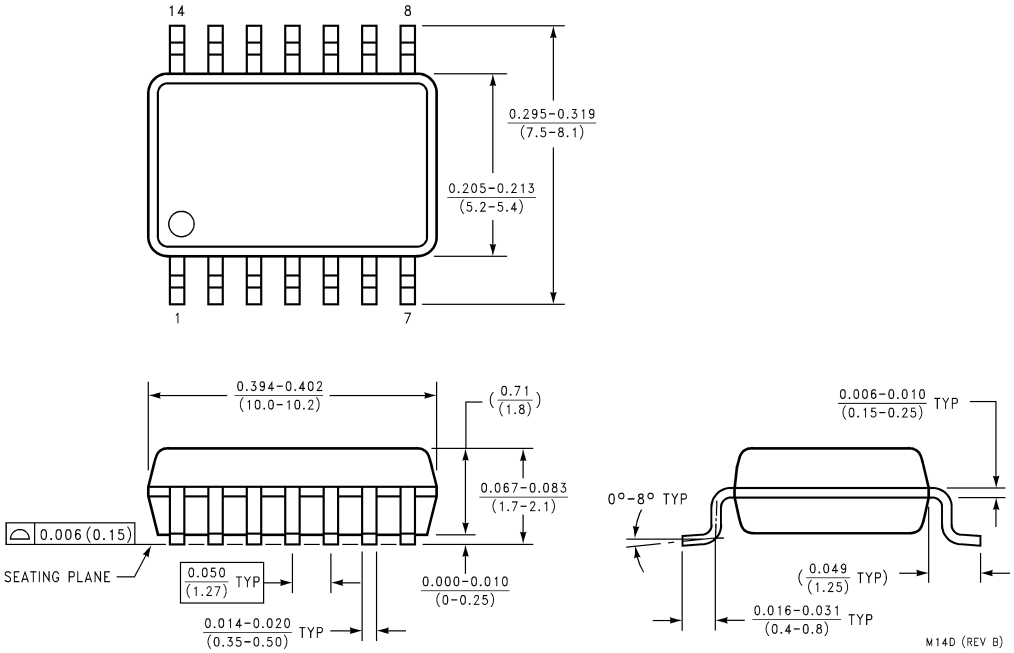


Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Small Outline Package, SOIC EIAJ
Package Number M14D

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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April 1998

FAIRCHILD SEMICONDUCTOR™

74LVQ04
Low Voltage Hex Inverter

General Description

The LVQ04 contains six inverters.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

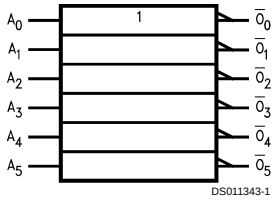
Ordering Code:

Ordering Number	Package Number	Package Description
74LVQ04SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ04SJ	M14D	14-Lead Molded Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

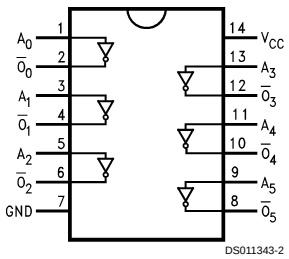
IEEE/IEC



DS011343-1

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011343-2

Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.8	1.1		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.8	−1.1		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}) 0V to threshold (V_{IHD}) f = 1 MHz.

AC Electrical Characteristics

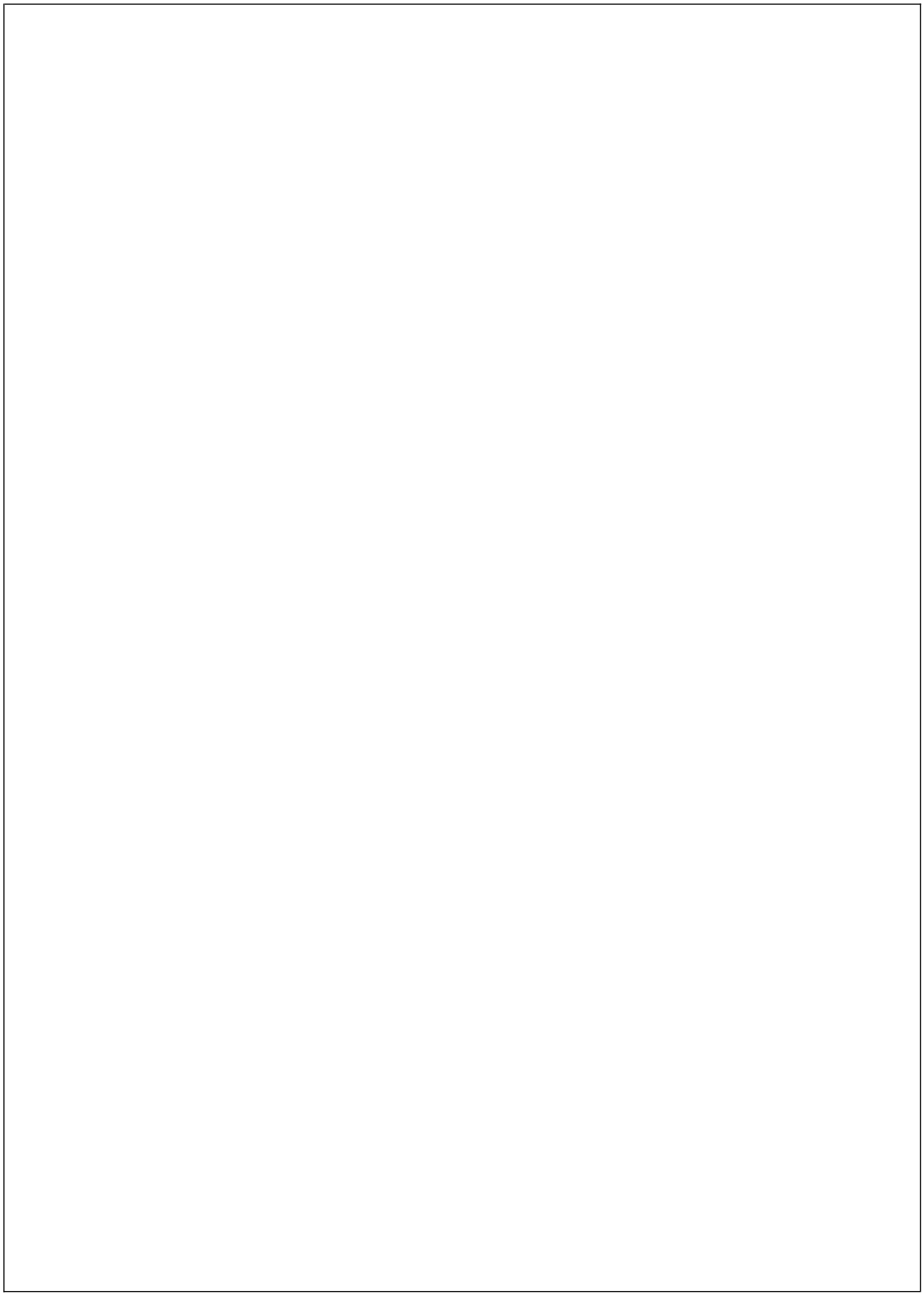
Symbol	Parameter	V_{CC} (V)	$T_A = +25^\circ C$, $C_L = 50$ pF			$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	5.4	12.7	1.0	14.0	ns
		3.3 ±0.3	1.5	4.5	9.0	1.0	10.0	
t_{PHL}	Propagation Delay	2.7	1.5	5.4	12.0	1.0	12.0	ns
		3.3 ±0.3	1.5	4.5	8.5	1.0	9.5	
t_{OSHL}	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

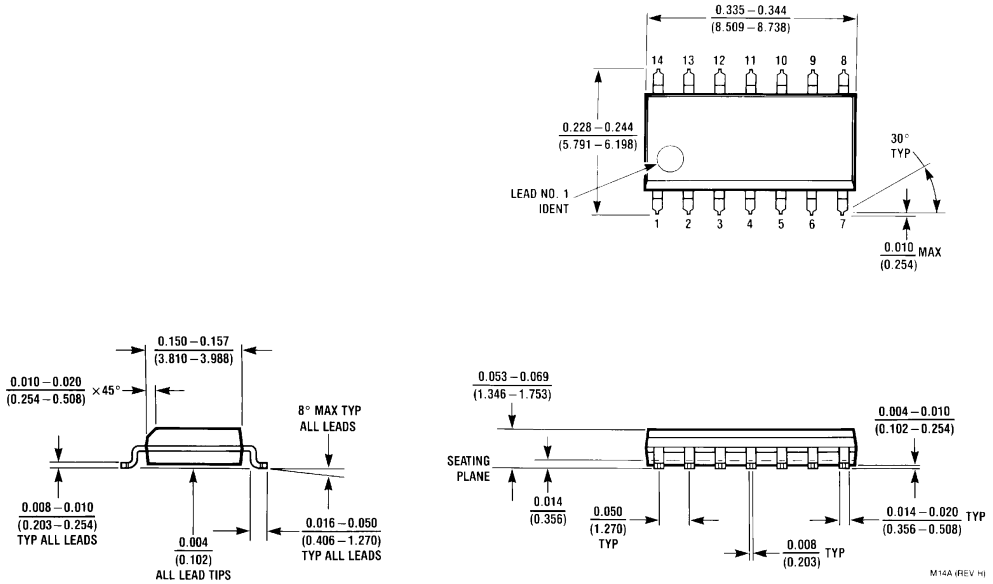
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	17	pF	V_{CC} = 3.3V

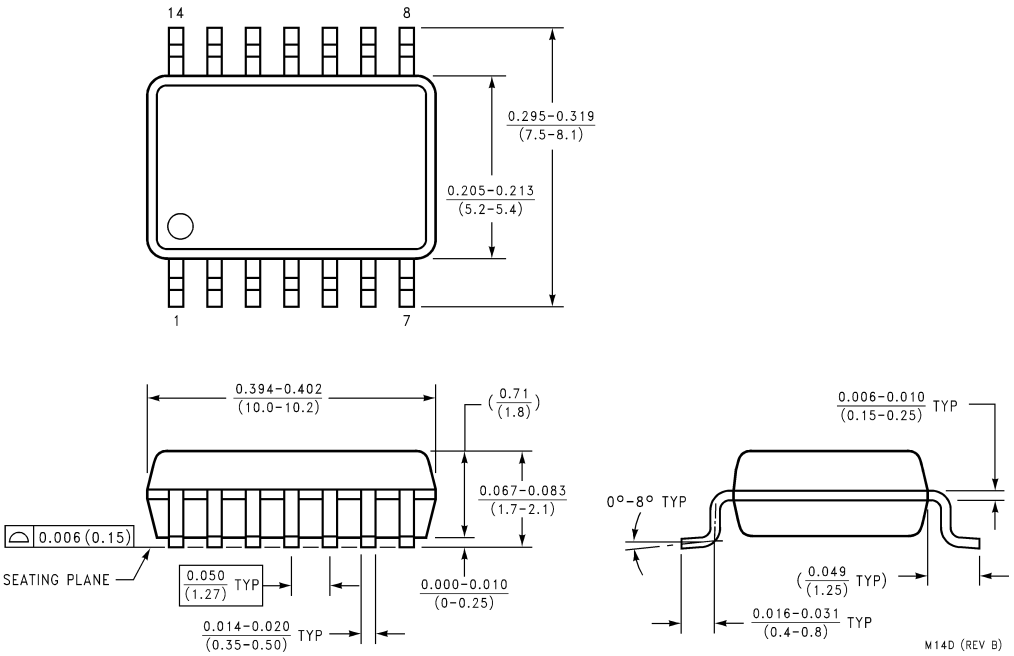
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Small Outline Package, SOIC JEDEC
Package Number M14A



14-Lead Molded Small Outline Package, SOIC EIAJ
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1998

74LVQ08
Low Voltage Quad 2-Input AND Gate

General Description

The LVQ08 contains four, 2-input AND gates.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

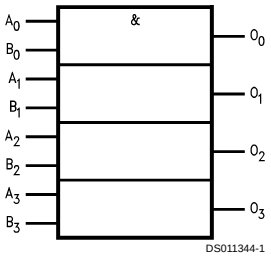
Ordering Code:

Order Number	Package Number	Package Description
74LVQ08SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ08SJ	M14D	14-Lead Molded Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

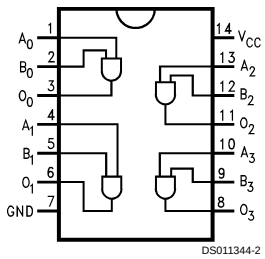
IEEE/IEC



DS011344-1

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011344-2

Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V
V_{OH}	Minimum High Level	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
	Output Voltage	3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
	Output Voltage	3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}	Output Current (Note 4)	3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.8	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.8	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

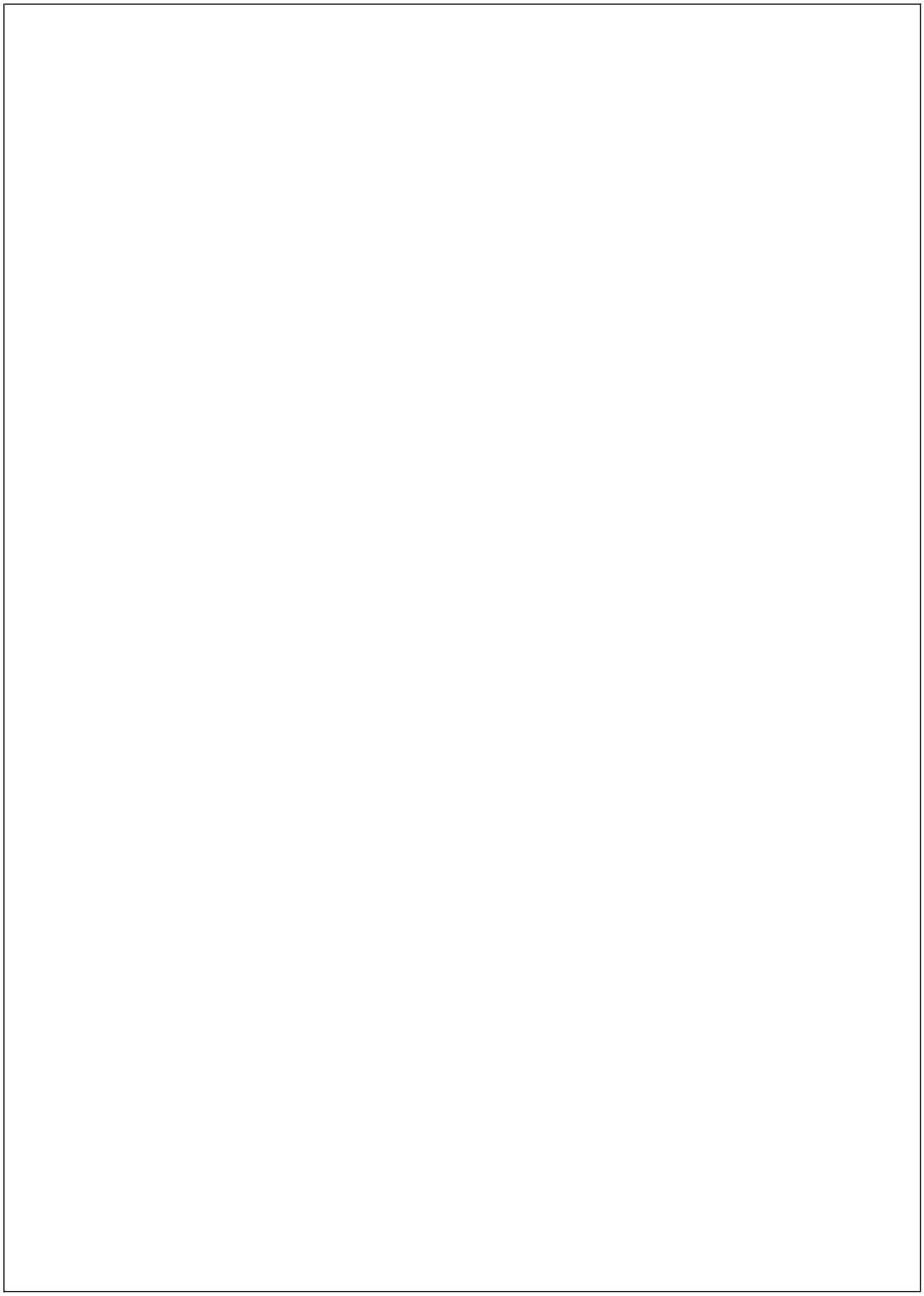
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	9.0	13.4	1.0	14.0	ns
		3.3 ±0.3	1.5	7.5	9.5	1.0	10.0	
t_{PHL}	Propagation Delay	2.7	1.5	8.4	12.0	1.0	13.0	ns
		3.3 ±0.3	1.5	7.0	8.5	1.0	9.0	
t_{OSHL}	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	(Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

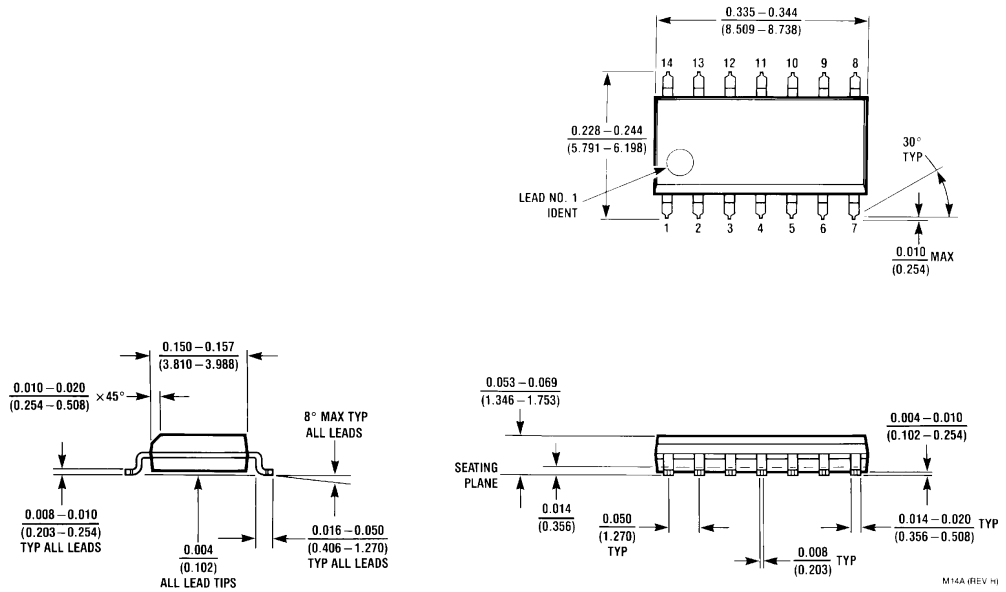
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	17	pF	V_{CC} = 3.3V

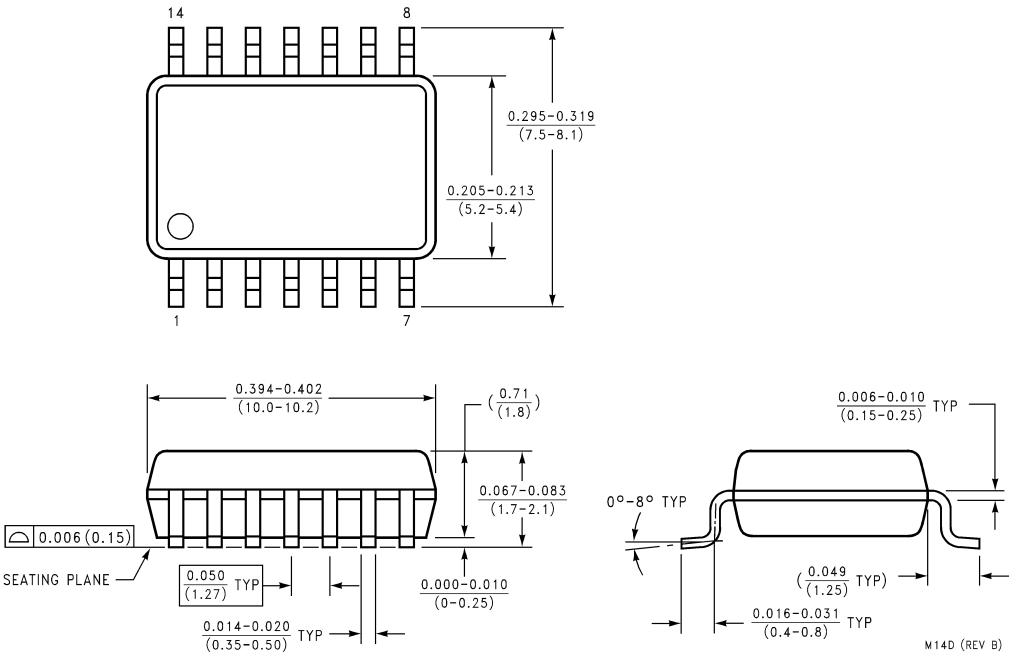
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Small Outline Package, SOIC JEDEC
Package Number M14A



14-Lead Molded Small Outline Package, SOIC EIAJ
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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May 1998

74LVQ125
Low Voltage Quad Buffer with 3-STATE Outputs

General Description

The LVQ125 contains four independent non-inverting buffers with 3-STATE outputs.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

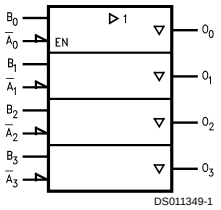
Ordering Code:

Order Number	Package Number	Package Description
74LVQ125SC	M14A	14-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
74LVQ125SJ	M14D	14-Lead Small Outline Package, SOIC EIAJ

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

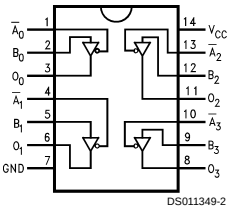
IEEE/IEC



DS011349-1

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011349-2

Pin Descriptions

Pin Names	Description
$\overline{A}_n$, B_n	Inputs
O_n	Outputs

Truth Table

Inputs		Output
$\overline{A}_n$	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteritics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85° C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Min (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.6	1.0		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.6	−1.0		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.5	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

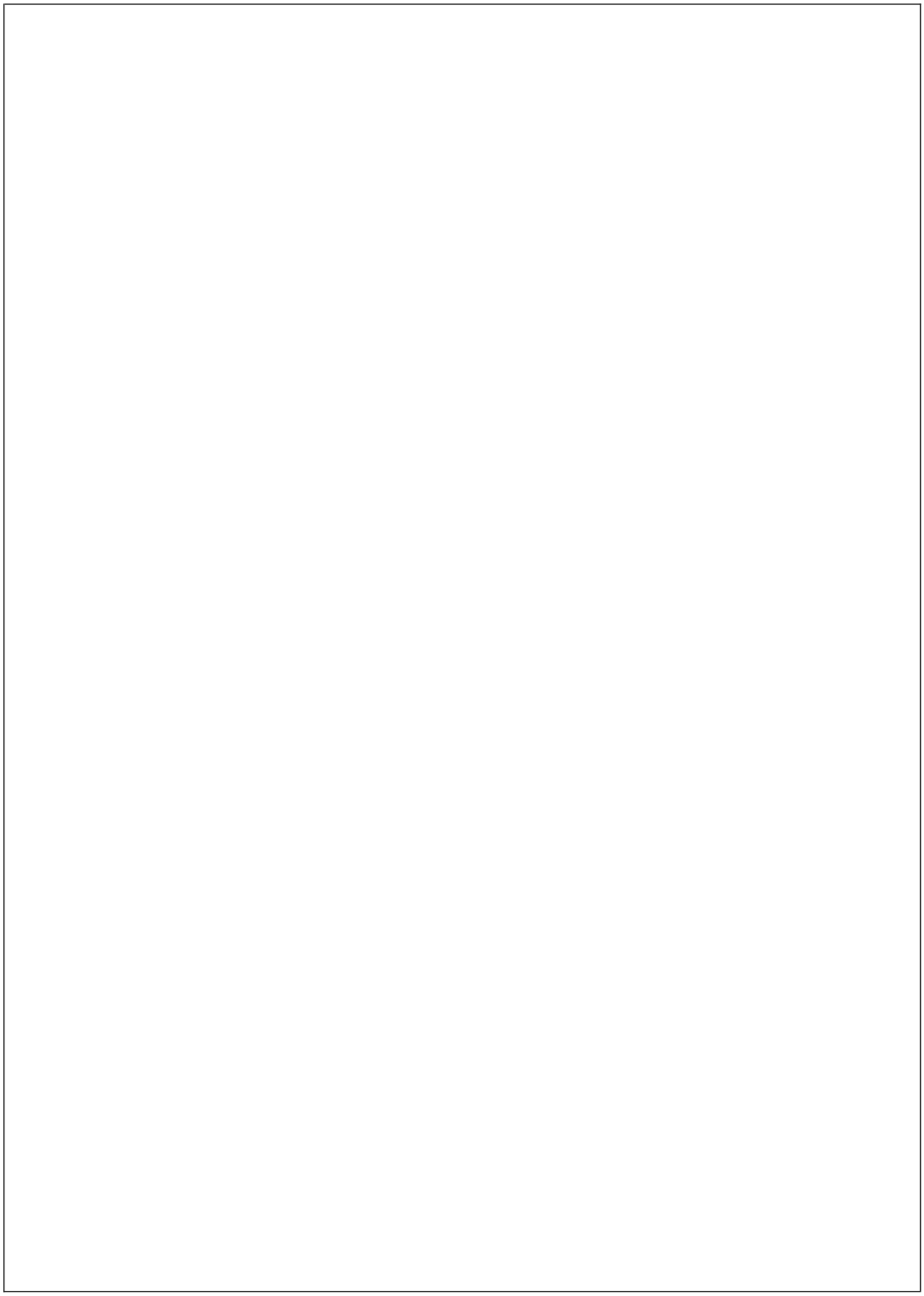
Symbol	Parameter	V_{CC} (V)	T_A = +25˚C, C_L = 50 pF			T_A = −40˚C to +85˚C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.0	7.8	12.7	1.0	14.0	ns
	Data to Output	3.3 ±0.3	1.0	6.5	9.0	1.0	10.0	
t_{PHL}	Propagation Delay	2.7	1.0	7.8	12.7	1.0	14.0	ns
	Data to Output	3.3 ±0.3	1.0	6.5	9.0	1.0	10.0	
t_{PZH}	Output Enable Time	2.7	1.0	7.2	14.8	1.0	16.0	ns
		3.3 ±0.3	1.0	6.0	10.5	1.0	11.0	
t_{PZL}	Output Enable Time	2.7	1.0	9.0	14.0	1.0	16.0	ns
		3.3 ±0.3	1.0	7.5	10.0	1.0	11.0	
t_{PHZ}	Output Disable Time	2.7	1.0	9.0	14.0	1.0	15.0	ns
		3.3 ±0.3	1.0	7.5	10.0	1.0	10.5	
t_{PLZ}	Output Disable Time	2.7	1.0	9.0	14.8	1.0	16.5	ns
		3.3 ±0.3	1.0	7.5	10.5	1.0	11.5	
$t_{OSHL,}$	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

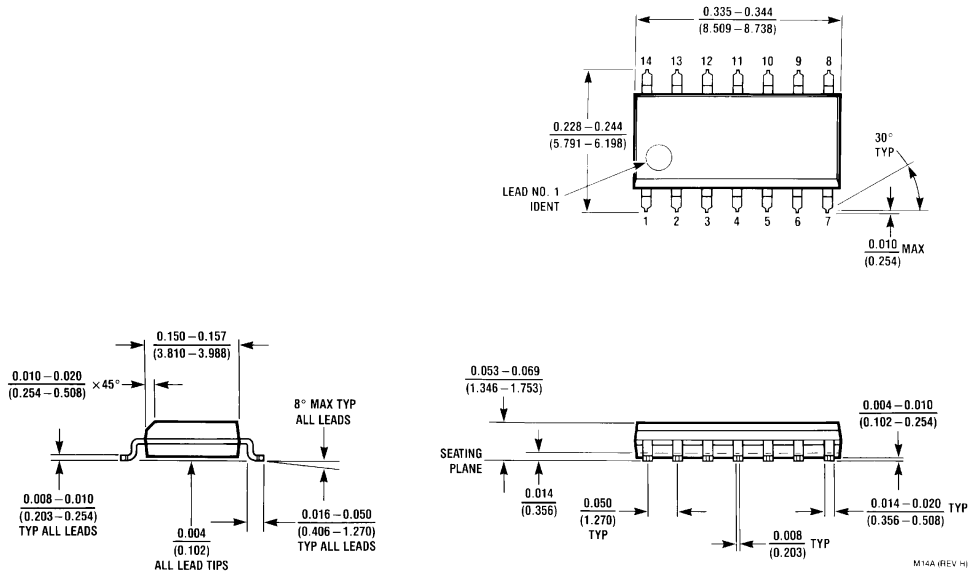
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	34	pF	V_{CC} = 3.3V

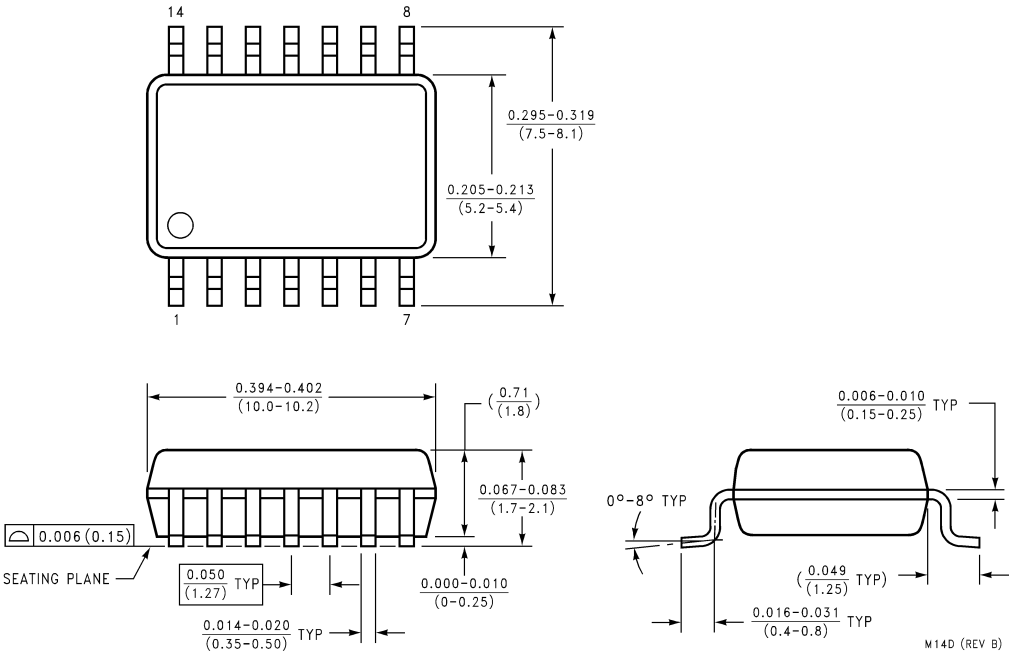
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Small Outline Integrated Circuit
Package Number M14A



14-Lead Small Outline Package EIAJ
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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May 1998

FAIRCHILD SEMICONDUCTOR TM

74LVQ138
Low Voltage 1-of-8 Decoder/Demultiplexer

General Description

The LVQ138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed bipolar memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three LVQ138 devices or a 1-of-32 decoder using four LVQ138 devices and one inverter.

Features

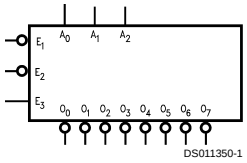
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity
- Demultiplexing capability
- Multiple input enable for each expansion
- Active LOW mutually exclusive outputs

Ordering Code:

Order Number	Package Number	Package Description
74LVQ138SC	M16A	16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
74LVQ138SJ	M16D	16-Lead Molded Small Outline Package, SOIC EIAJ

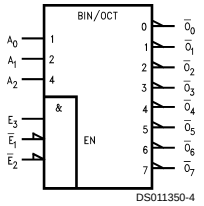
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011350-1

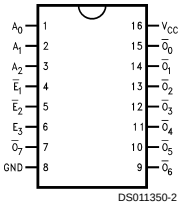
IEEE/IEC



DS011350-4

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011350-2

Pin Descriptions

Pin Names	Description
A_0–A_2	Address Inputs
$\overline{E}_1$–$\overline{E}_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0$–$\overline{O}_7$	Outputs

Functional Description

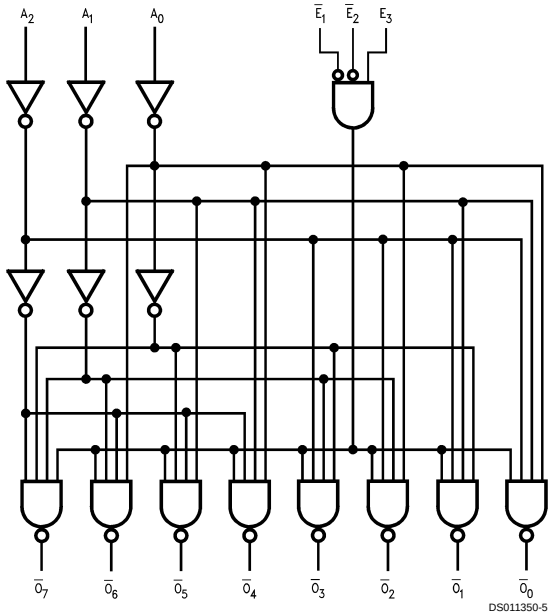
The LVQ138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A_0, A_1, A_2) and, when enabled, provides eight mutually exclusive active-LOW outputs ($\overline{O}_0$–$\overline{O}_7$). The LVQ138 features three Enable inputs, two active-LOW ($\overline{E}_1$, $\overline{E}_2$) and one active-HIGH (E_3). All outputs will be HIGH unless $\overline{E}_1$ and $\overline{E}_2$ are LOW and E_3 is HIGH. This multiple enable function allows easy parallel expansion of the device to a 1-of-32 (5 lines to 32 lines) decoder with just four LVQ138 devices and one inverter (see *Figure 1*). The LVQ138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active-HIGH or active-LOW state.

Truth Table

Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



DS011350-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Logic Diagram

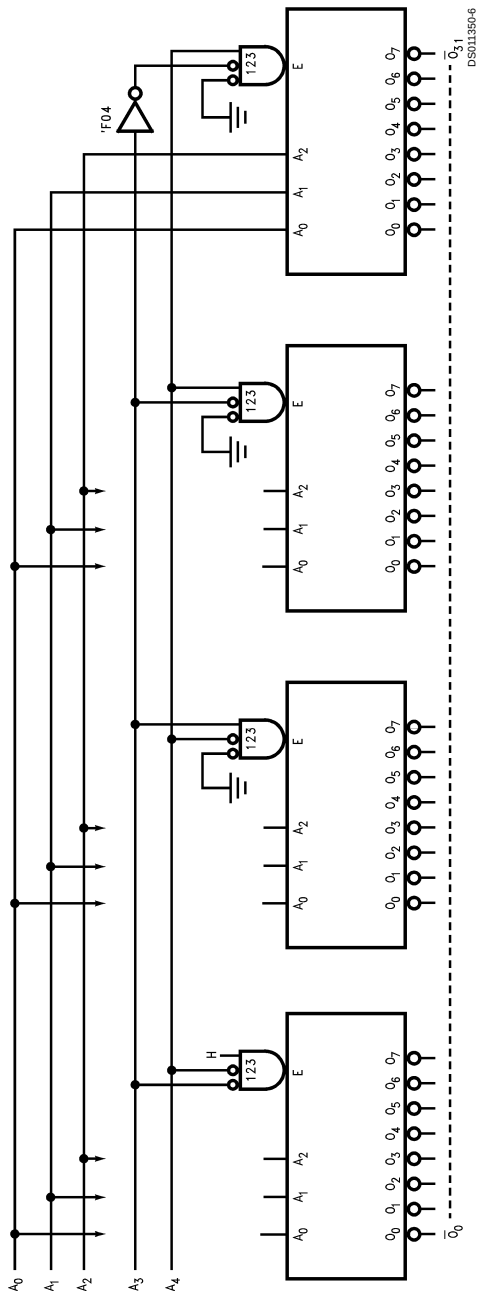


FIGURE 1. Expansion to 1-of-32 Decoding

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C		T_A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Outut Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OH}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.7	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

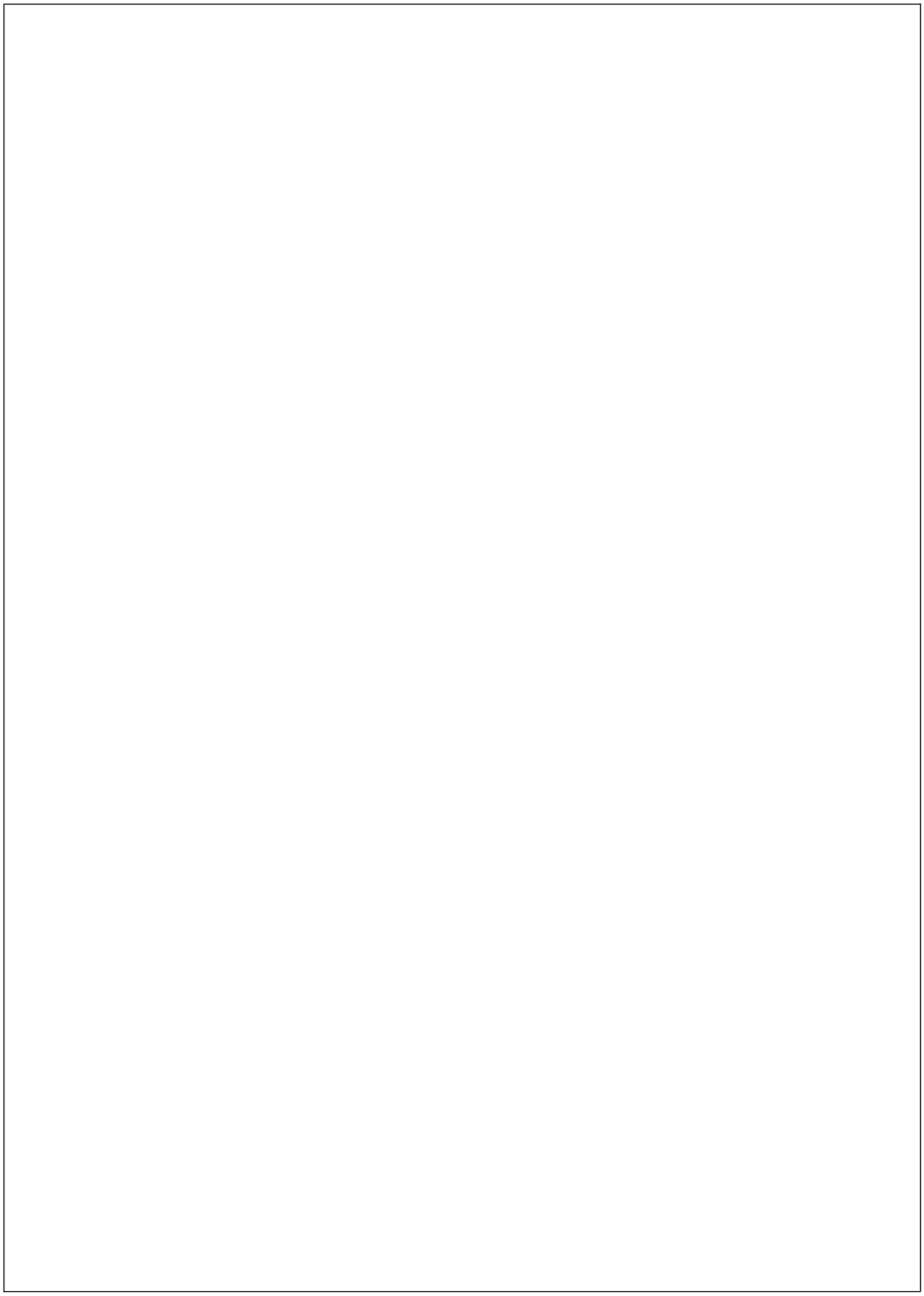
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	10.2	18.3	1.5	21.0	ns
	A_n to $\overline{O}_n$	3.3 ±0.3	1.5	8.5	13.0	1.5	15.0	
t_{PHL}	Propagation Delay	2.7	1.5	9.6	17.6	1.5	20.0	ns
	A_n to $\overline{O}_n$	3.3 ±0.3	1.5	8.0	12.5	1.5	14.0	
t_{PLH}	Propagation Delay	2.7	1.5	13.2	21.0	1.5	23.0	ns
	$\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	3.3 ±0.3	1.5	11.0	15.0	1.5	16.0	
t_{PHL}	Propagation Delay	2.7	1.5	11.4	19.0	1.5	21.0	ns
	$\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	3.3 ±0.3	1.5	9.5	13.5	1.5	15.0	
t_{PLH}	Propagation Delay	2.7	1.5	13.2	21.8	1.5	23.5	ns
	E_3 to $\overline{O}_n$	3.3 ±0.3	1.5	11.0	15.5	1.5	16.5	
t_{PHL}	Propagation Delay	2.7	1.5	10.2	18.3	1.5	20.0	ns
	E_3 to $\overline{O}_n$	3.3 ±0.3	1.5	8.5	13.0	1.5	14.0	
t_{OSHL},	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

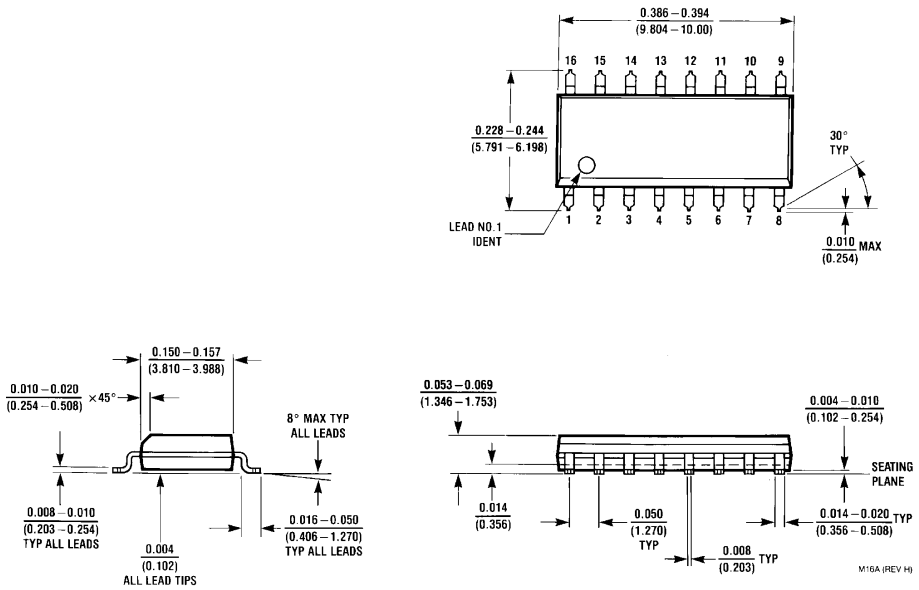
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	45	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

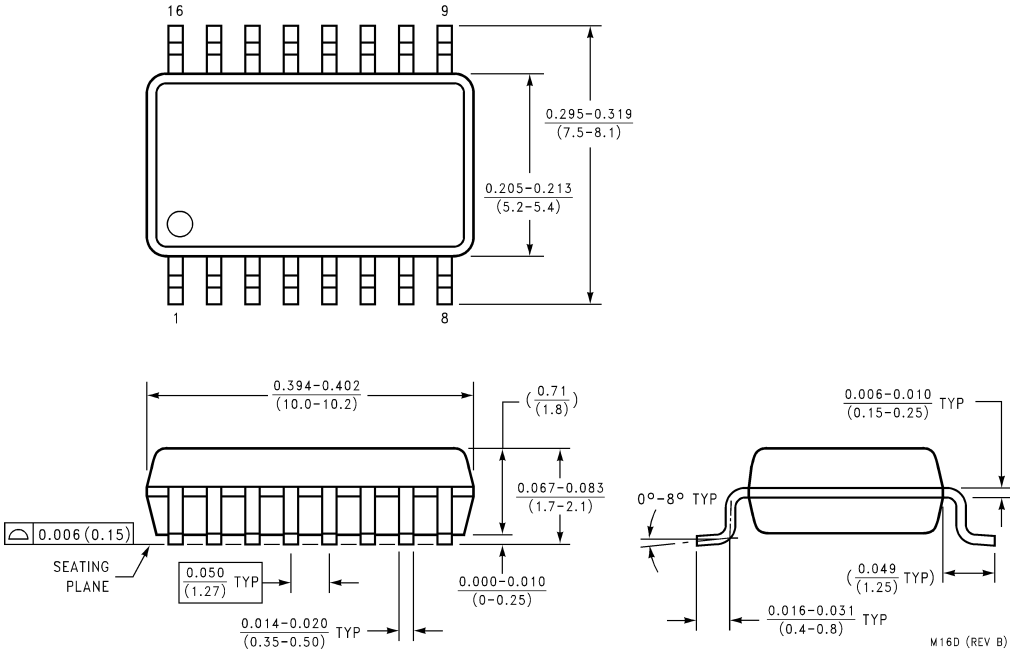


Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead (0.150" Wide) Small Outline Integrated Circuit
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Molded Small Outline Package
Package Number M16D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ14
Low Voltage Hex Inverter with Schmitt Trigger Input

General Description

The LVQ14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVQ14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

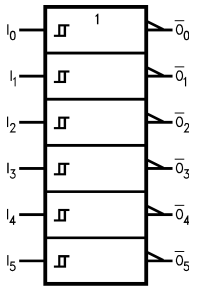
Ordering Code:

Order Number	Package Number	Package Description
74LVQ14SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
74LVQ14SJ	M14D	14-Lead Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

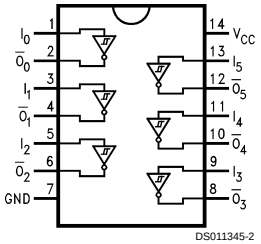
IEEE/IEC



DS011345-1

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011345-2

Pin Descriptions

Pin Names	Description
I_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

Input	Output
I	$\overline{O}$
L	H
H	L

H = High Voltage Level
L = Low Voltage Level

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	
LVQ	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
V_{t+}	Maximum Positive Threshold	3.0		2.2	2.2	V	T_A = Worst Case
V_{t-}	Minimum Negative Threshold	3.0		0.5	0.5	V	T_A = Worst Case
$V_{h(max)}$	Maximum Hysteresis	3.0		1.2	1.2	V	T_A = Worst Case
$V_{h(min)}$	Minimum Hysteresis	3.0		0.3	0.3	V	T_A = Worst Case
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.9	1.1		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.8	−1.1		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.9	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.3	2.0		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

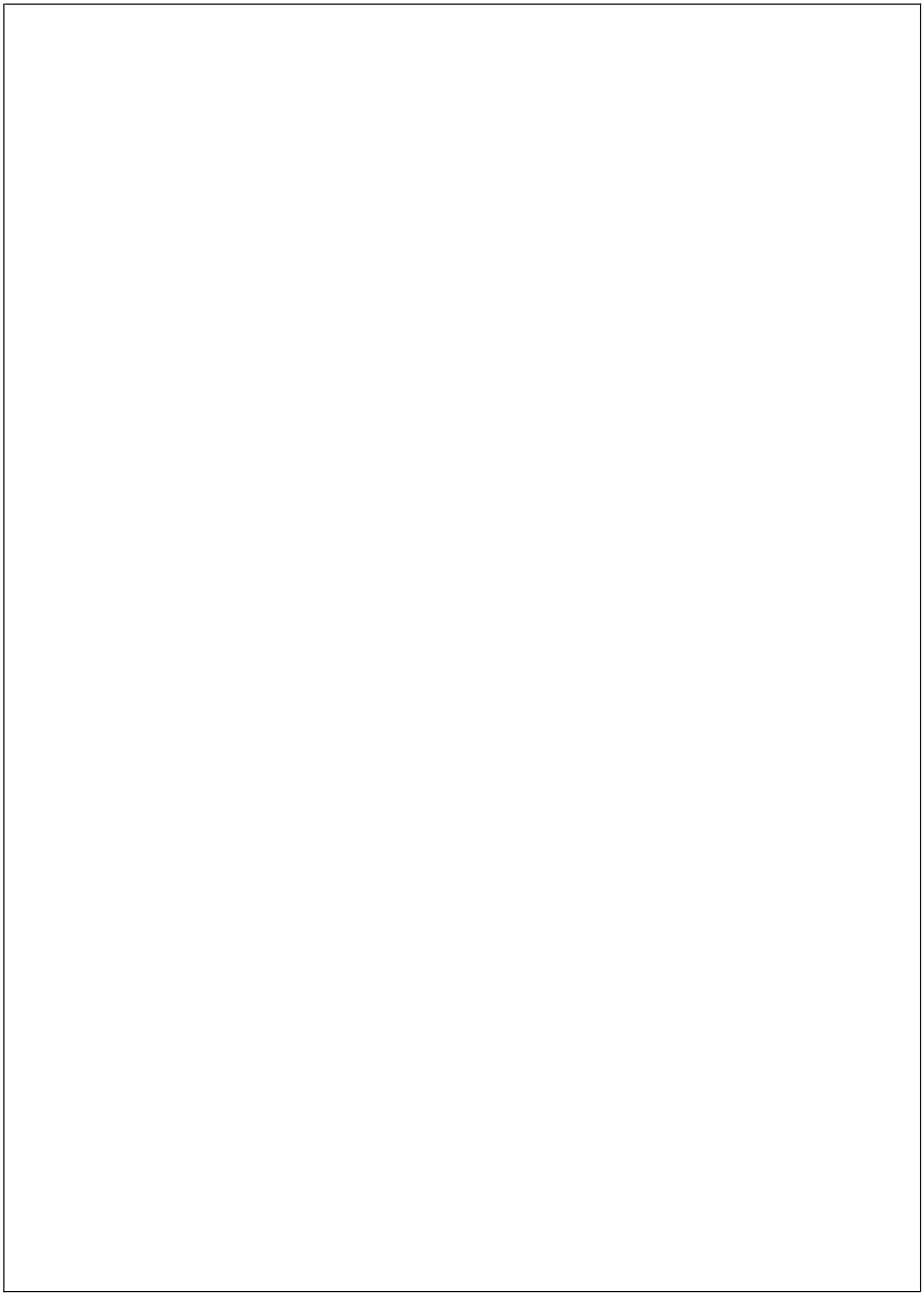
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	11.4	19.0	1.5	21.0	ns
		3.3 ±0.3	1.5	9.5	13.5	1.5	15.0	
t_{PHL}	Propagation Delay	2.7	1.5	9.0	16.2	1.5	19.0	ns
		3.3 ±0.3	1.5	7.5	11.5	1.5	13.0	
t_{OSHL},	Output to Output	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Skew (Note 9)	3.3 ±0.3		1.0	1.5		1.5	
	Data to Output							

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

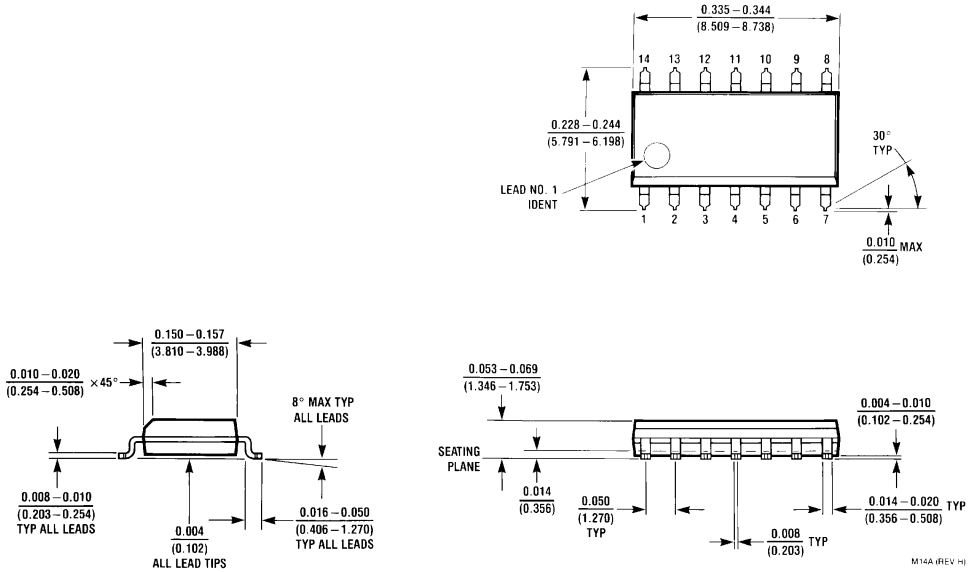
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	20	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

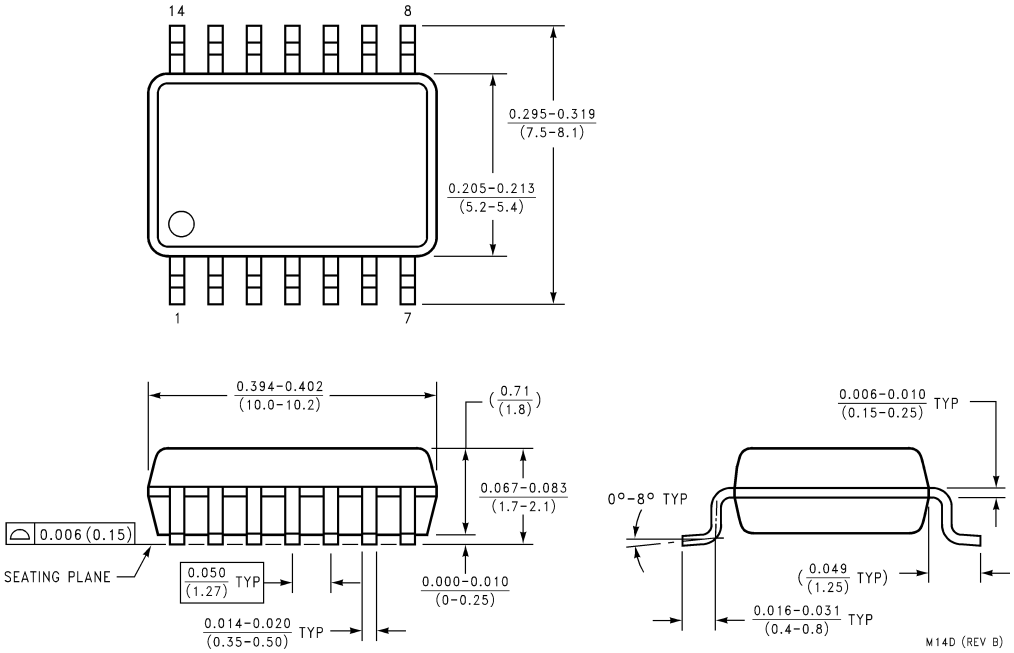


Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Small Outline Package, SOIC EIAJ
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ151
Low Voltage 8-Input Multiplexer

General Description

The LVQ151 is a high-speed 8-input digital multiplexer. It provides, in one package, the ability to select one line of data from up to eight sources. The LVQ151 can be used as a universal function generator to generate any logic function of four variables. Both true and complementary outputs are provided.

Features

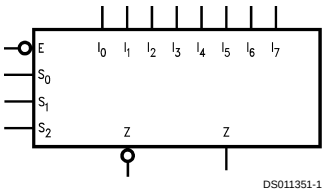
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

Ordering Code:

Order Number	Package Number	Package Description
74LVQ151SC	M16A	16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
74LVQ151SJ	M16D	16-Lead Molded Small Outline Package, SOIC EIAJ

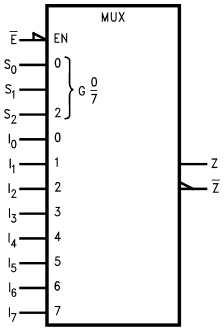
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011351-1

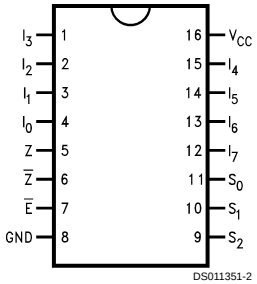
IEEE/IEC



DS011351-4

Connection Diagram

Pin Assignment
SOIC JEDEC and EIAJ



DS011351-2

Pin Descriptions

Pin Names	Description
I_0–I_7	Data Inputs
S_0–S_2	Select Inputs
$\overline{E}$	Enable Input
Z	Data Output
$\overline{Z}$	Inverted Data Output

Truth Table

Inputs				Outputs	
$\overline{E}$	S_2	S_1	S_0	$\overline{Z}$	Z
H	X	X	X	H	L
L	L	L	L	$\overline{I}_0$	I_0
L	L	L	H	$\overline{I}_1$	I_1
L	L	H	L	$\overline{I}_2$	I_2
L	L	H	H	$\overline{I}_3$	I_3
L	H	L	L	$\overline{I}_4$	I_4
L	H	L	H	$\overline{I}_5$	I_5
L	H	H	L	$\overline{I}_6$	I_6
L	H	H	H	$\overline{I}_7$	I_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

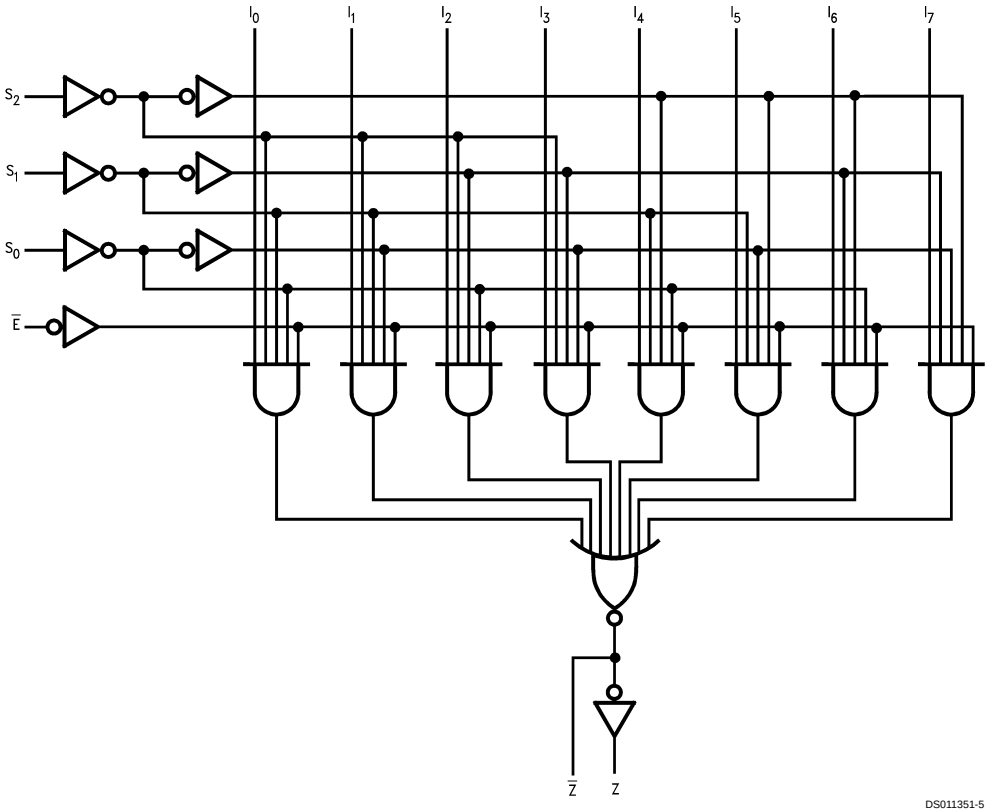
Functional Description

The LVQ151 is a logic implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0, S_1, S_2. Both true and complementary outputs are provided. The Enable input ($\overline{E}$) is active LOW. When it is not activated, the complementary output is HIGH and the true output is LOW regardless of all other inputs. The logic function provided at the output is:

$$Z = \overline{E} \bullet (I_0 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_1 \bullet S_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_2 \bullet \overline{S}_0 \bullet S_1 \bullet \overline{S}_2 + I_3 \bullet S_0 \bullet S_1 \bullet \overline{S}_2 + I_4 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet S_2 + I_5 \bullet S_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_6 \bullet \overline{S}_0 \bullet S_1 \bullet S_2 + I_7 \bullet S_0 \bullet S_1 \bullet \overline{S}_2)$$

The LVQ151 provides the ability, in one package to select from eight sources of data or control information. By proper manipulation of the inputs, the LVQ151 can provide any logic function of four variables and its complement.

Logic Diagram



DS011351-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings.The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}	Output Current (Note 4)	3.6			−25	mA	V_{OHD} = 2.0V (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.7	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	3.0	13.8	25.3	3.0	28.0	ns
	S_n to Z or $\overline{Z}$	3.3 ±0.3	3.0	11.5	18.0	3.0	20.0	
t_{PHL}	Propagation Delay	2.7	2.5	14.4	25.3	2.5	28.0	ns
	S_n to Z or $\overline{Z}$	3.3 ±0.3	2.5	12.0	18.0	2.5	20.0	
t_{PLH}	Propagation Delay	2.7	2.5	9.6	18.3	2.0	20.0	ns
	$\overline{E}$ to Z or $\overline{Z}$	3.3 ±0.3	2.5	8.0	13.0	2.0	14.0	
t_{PHL}	Propagation Delay	2.7	1.5	10.2	18.3	1.5	20.0	ns
	$\overline{E}$ to Z or $\overline{Z}$	3.3 ±0.3	1.5	8.5	13.0	1.5	14.0	
t_{PLH}	Propagation Delay	2.7	2.5	11.4	19.7	2.0	22.0	ns
	I_n to Z or $\overline{Z}$	3.3 ±0.3	2.5	9.5	14.0	2.0	15.5	
t_{PHL}	Propagation Delay	2.7	2.5	11.4	21.1	2.0	23.0	ns
	I_n to Z or $\overline{Z}$	3.3 ±0.3	2.5	9.5	15.0	2.0	16.0	
t_{OSHL}	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

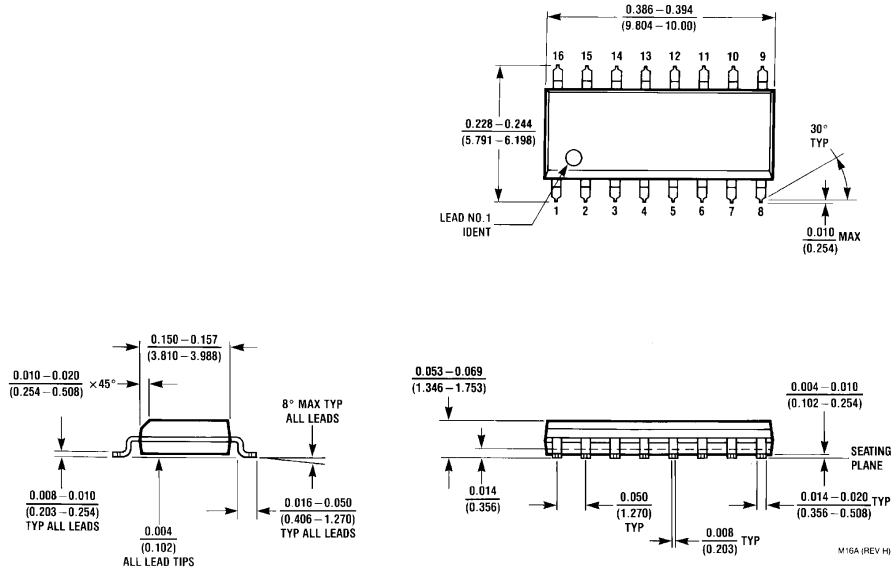
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

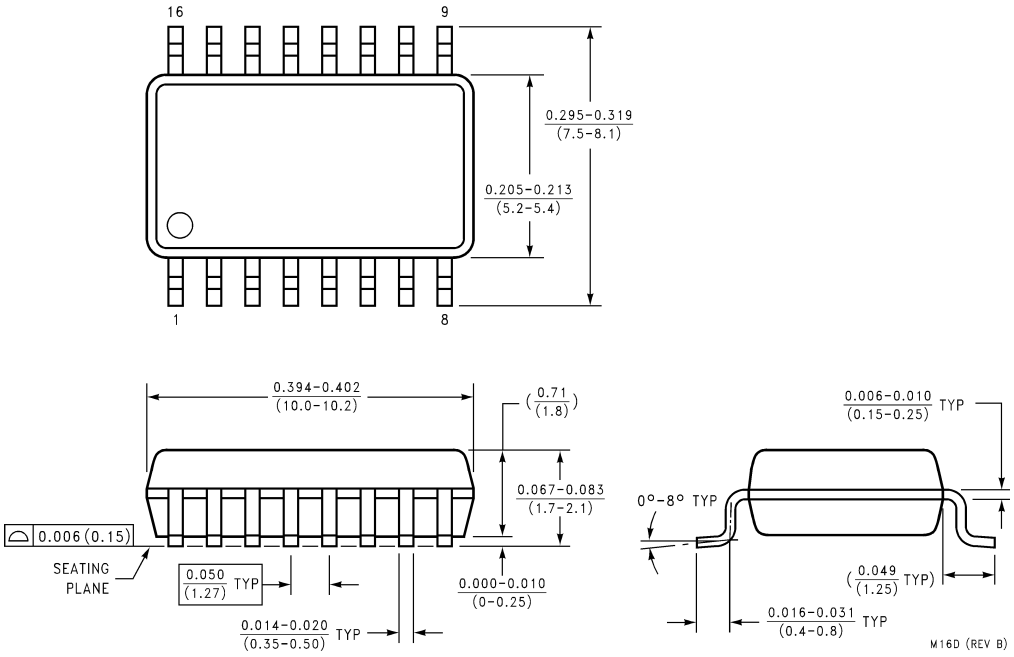
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	45	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
Package Number M16A



16-Lead Molded Small Outline Package, SOIC EIAJ
Package Number M16D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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May 1998

74LVQ157
Low Voltage Quad 2-Input Multiplexer

General Description

The LVQ157 is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (noninverted) form. The LVQ157 can also be used as a function generator.

Features

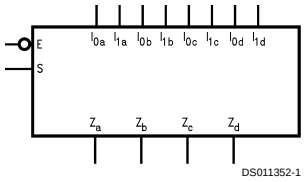
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω.

Ordering Code:

Order Number	Package Number	Package Description
74LVQ157SC	M16A	16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
74LVQ157SJ	M16D	16-Lead Molded Small Outline Package, SOIC EIAJ

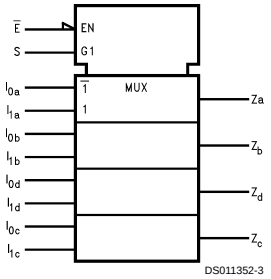
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011352-1

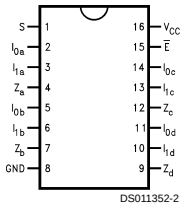
IEEE/IEC



DS011352-3

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011352-2

Pin Descriptions

Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{E}$	Enable Input
S	Select Input
Z_a–Z_d	Outputs

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

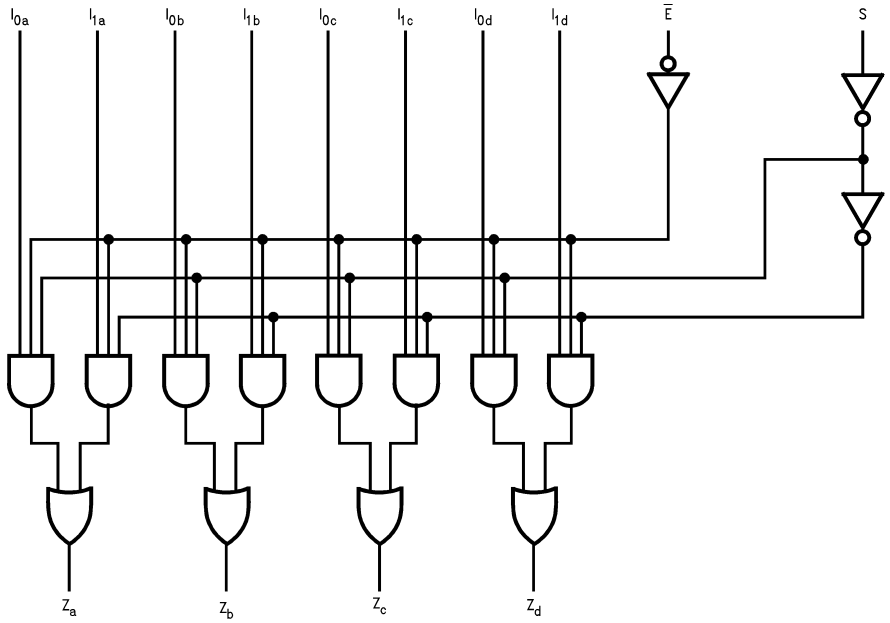
Functional Description

The LVQ157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\overline{E}$) is active-LOW. When $\overline{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The LVQ157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$Z_a = \overline{E} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$
$Z_b = \overline{E} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$
$Z_c = \overline{E} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$
$Z_d = \overline{E} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$

A common use of the LVQ157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The LVQ157 can generate any four of the sixteen different functions of two variables with one variable common. This is useful for implementing gating functions.

Logic Diagram



DS011352-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}	Output Current (Note 4)	3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.7	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	84	16.2	1.5	19.0	ns
	S to Z_n	3.3 ±0.3	1.5	7.0	11.5	1.5	13.0	
t_{PHL}	Propagation Delay	2.7	1.5	7.8	15.5	1.5	17.0	ns
	S to Z_n	3.3 ±0.3	1.5	6.5	11.0	1.5	12.0	
t_{PLH}	Propagation Delay	2.7	1.5	8.4	16.2	1.5	19.0	ns
	$\overline{E}$ to Z_n	3.3 ±0.3	1.5	7.0	11.5	1.5	13.0	
t_{PHL}	Propagation Delay	2.7	1.5	7.8	15.5	1.5	17.0	ns
	$\overline{E}$ to Z_n	3.3 ±0.3	1.5	6.5	11.0	1.5	12.0	
t_{PLH}	Propagation Delay	2.7	1.5	6.0	12.0	1.0	13.0	ns
	I_n to Z_n	3.3 ±0.3	1.5	5.0	8.5	1.0	9.0	
t_{PHL}	Propagation Delay	2.7	1.5	6.0	11.3	1.0	13.0	ns
	I_n to Z_n	3.3 ±0.3	1.5	5.0	8.0	1.0	9.0	
$t_{OSHL,}$	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

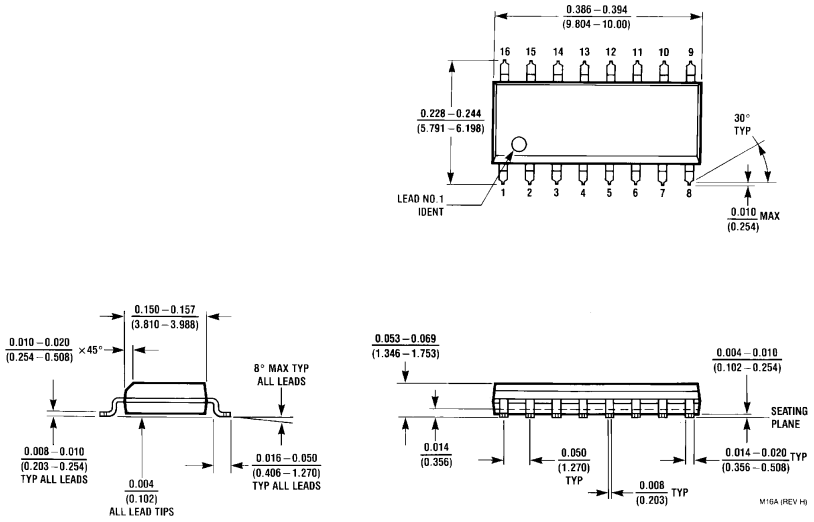
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

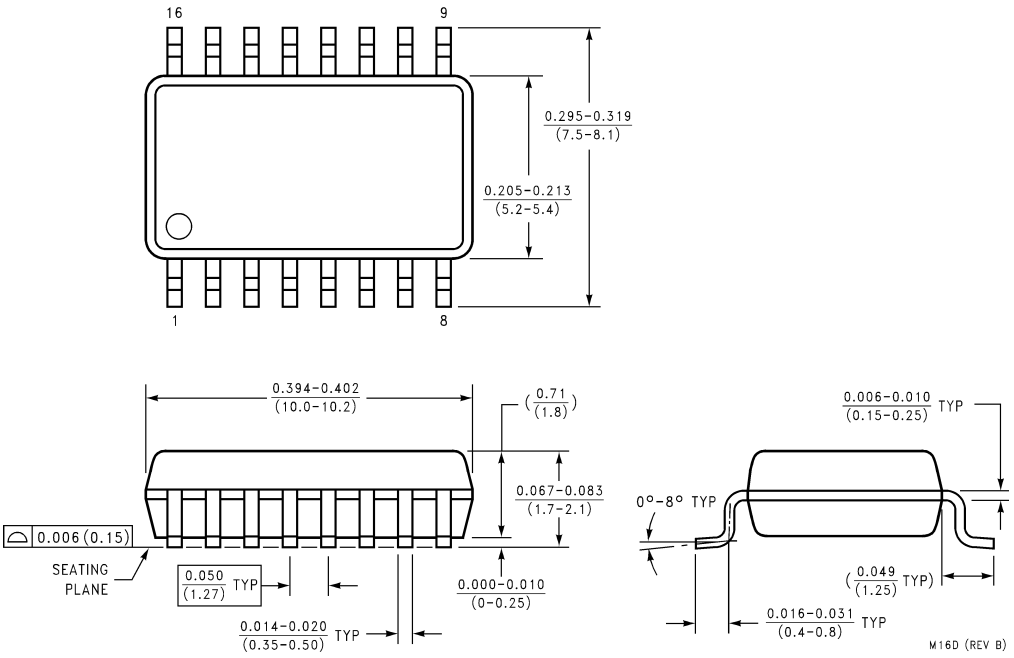
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_C = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	34.0	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
Package Number M16A



16-Lead Molded Small Outline Package, SOIC EIAJ
Package Number M16D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ174
Low Voltage Hex D-Type Flip-Flop with Master Reset

General Description

The LVQ174 is a high-speed hex D-type flip-flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the LOW-to-HIGH clock transition. The device has a Master Reset to simultaneously clear all flip-flops.

Features

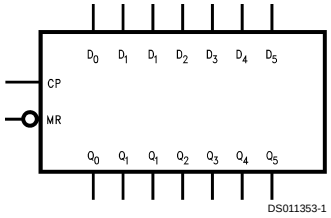
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

Ordering Code:

Order Number	Package Number	Package Description
74LVQ174SC	M16A	16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
74LVQ174SJ	M16D	16-Lead Molded Small Outline Package, SOIC EIAJ

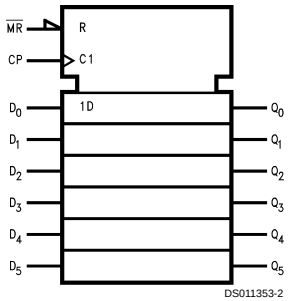
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011353-1

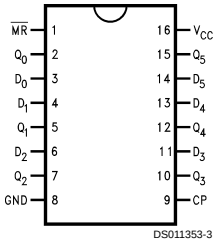
IEEE/IEC



DS011353-2

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011353-3

Pin Descriptions

Pin Names	Description
D_0–D_5	Data Inputs
CP	Clock Pulse Input
$\overline{MR}$	Master Reset Input
Q_0–Q_5	Outputs

Functional Description

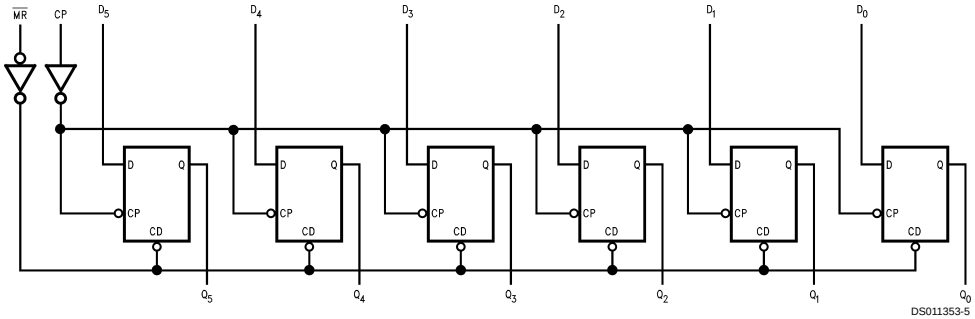
The LVQ174 consists of six edge-triggered D flip-flops with individual D inputs and Q outputs. The Clock (CP) and Master Reset ($\overline{MR}$) are common to all flip-flops. Each D input's state is transferred to the corresponding flip-flop's output following the LOW-to-HIGH Clock (CP) transition. A LOW input to the Master Reset ($\overline{MR}$) will force all outputs LOW independent of Clock or Data inputs. The LVQ174 is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Truth Table

Inputs			Output
$\overline{MR}$	CP	D	Q
L	X	X	L
H	⌐	H	H
H	⌐	L	L
H	L	X	Q

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



DS011353-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.7	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.6	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.8	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock	2.7	60	90		50		MHz
	Frequency	3.3 ±0.3	90	100		70		
t_{PLH}	Propagation Delay	2.7	2.0	10.8	16.2	1.5	18.0	ns
	CP to Q_n	3.3 ±0.3	2.0	9.0	11.5	1.5	12.5	
t_{PHL}	Propagation Delay	2.7	2.0	10.2	15.5	1.5	17.0	ns
	CP to Q_n	3.3 ±0.3	2.0	8.5	11.0	1.5	12.0	
t_{PHL}	Propagation Delay	2.7	2.5	10.8	16.2	2.0	18.0	ns
	$\overline{MR}$ to Q_n	3.3 ±0.3	2.5	9.0	11.5	2.0	12.5	
t_{OSHL},	Output to	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Output Skew (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

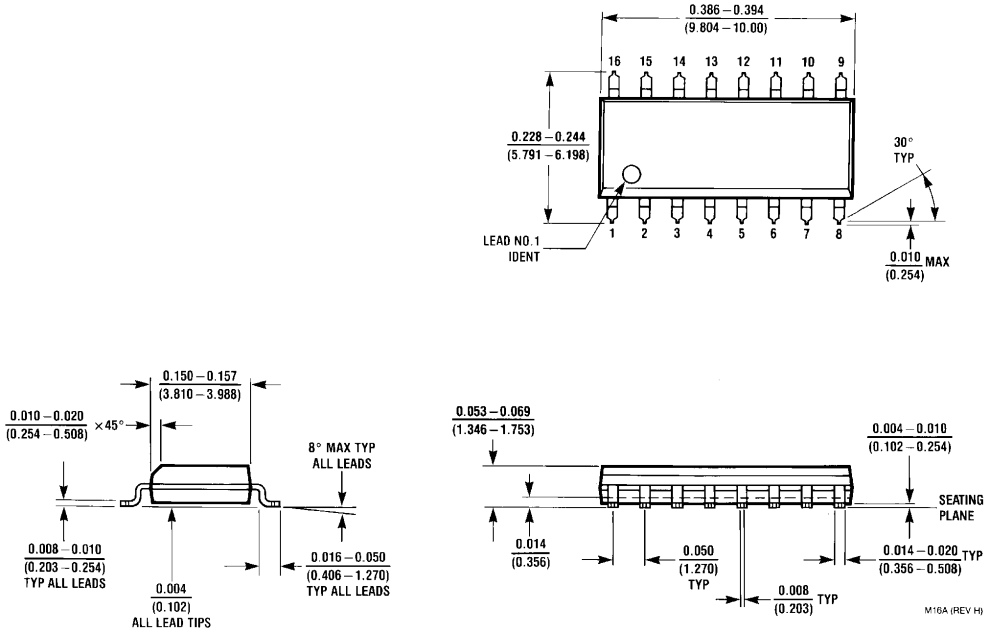
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF		T_A = −40°C to +85°C, C_L = 50 pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	2.7	3.0	8.0	10.0	ns
	D_n to CP	3.3 ±0.3	2.5	6.5	7.0	
t_H	Hold Time, HIGH or LOW	2.7	1.2	4.0	4.5	ns
	D_n to CP	3.3 ±0.3	1.0	3.0	3.0	
t_W	$\overline{MR}$ Pulse Width, LOW	2.7	1.2	7.0	10.0	ns
		3.3 ±0.3	1.0	5.5	7.0	
t_W	CP Pulse Width	2.7	1.2	7.0	10.0	ns
		3.3 ±0.3	1.0	5.5	7.0	
t_{rec}	Recovery Time	2.7	0	3.5	3.5	ns
	$\overline{MR}$ to CP	3.3 ±0.3	0	2.5	2.5	

Capacitance

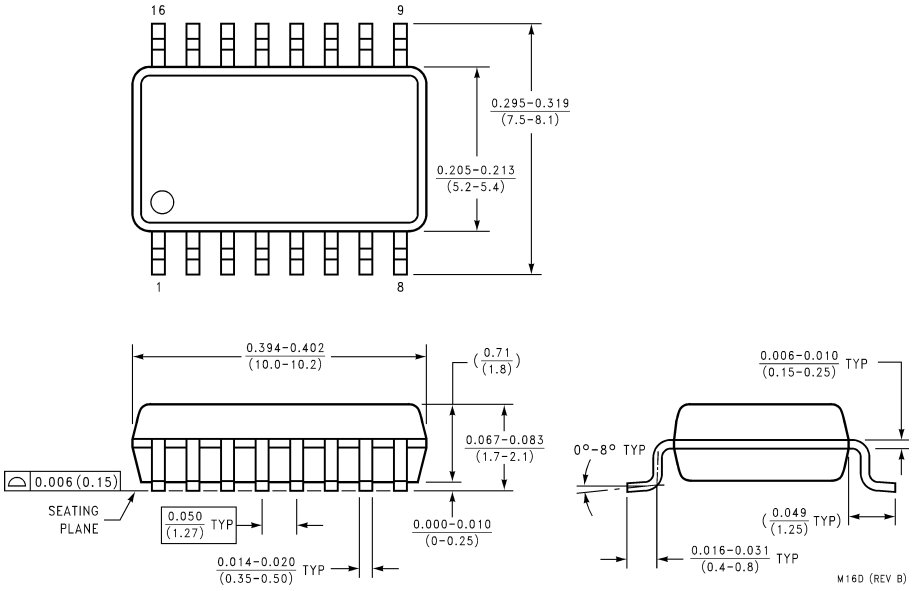
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	23	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted



16-Lead (0.150" Wide) Small Outline Integrated Circuit, SOIC JEDEC
Package Number M16A



16-Lead Molded Small Outline Package, SOIC EIAJ
Package Number M16D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ240
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVQ240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ, and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

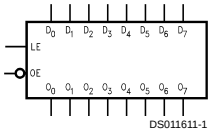
Ordering Code:

Order Number	Package Number	Package Description
74LVQ240SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
74LVQ240SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC, EIAJ
74LVQ240QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



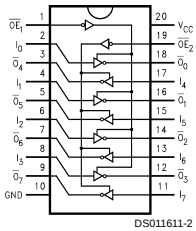
DS011611-1

Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Connection Diagram

Pin Assignment, SOIC and QSOP



DS011611-2

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level L = LOW Voltage Level
X = Immaterial Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data Inputs are driven 0V to 3.3V. One output @ GND.

Note 8: Max number of Data Inputs (n) switching. n−1 Inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

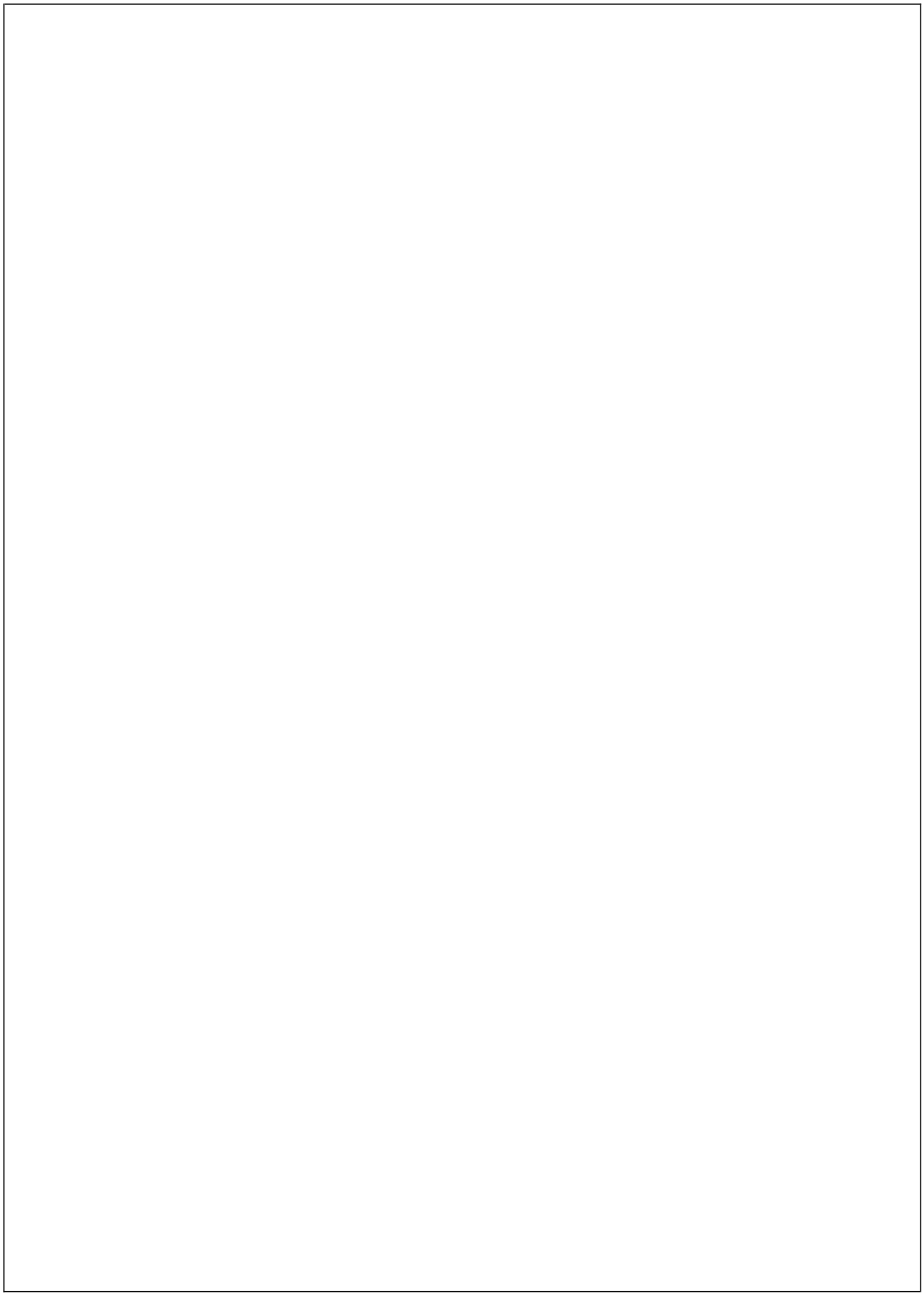
Symbol	Parameter	V_{CC} (V)	$T_A = +25^{\circ}C$, $C_L = 50$ pF			$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.0	8.4	14.0	2.0	15.0	ns
t_{PLH}	Data to Output	3.3 ±0.3	2.0	7.0	10.0	2.0	10.5	
t_{PZL}	Output Enable Time	2.7	2.5	9.6	16.9	2.5	18.0	ns
t_{PZH}		3.3±0.3	2.5	8.0	12.0	2.5	12.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.2	19.0	1.0	20.0	ns
t_{PLZ}		3.3 ±0.3	1.0	8.5	13.5	1.0	14.0	
t_{OSHL}	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

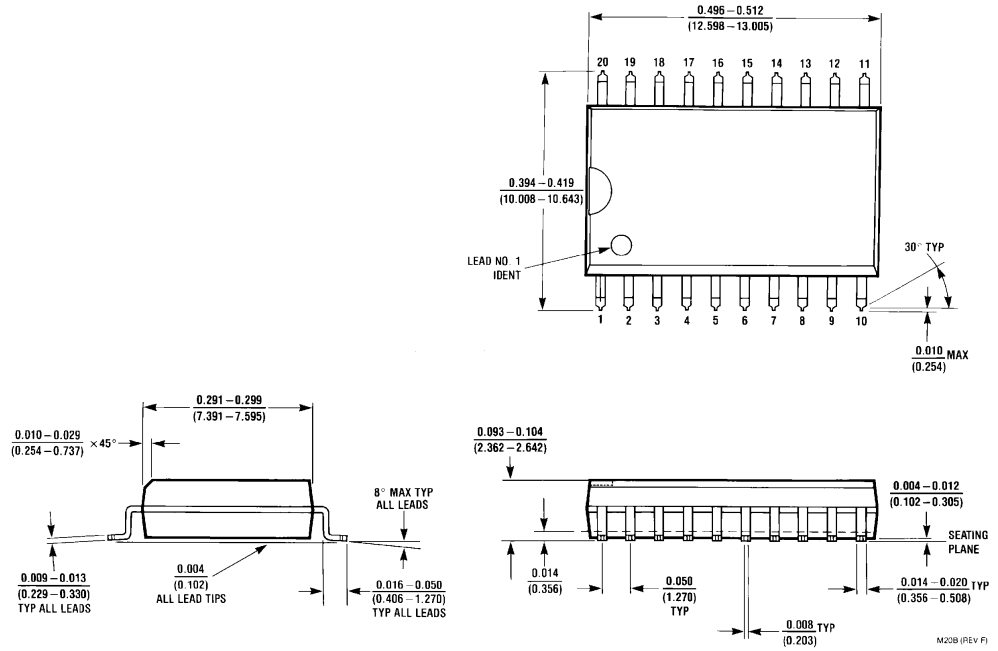
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	70	pF	V_{CC} = 3.3V

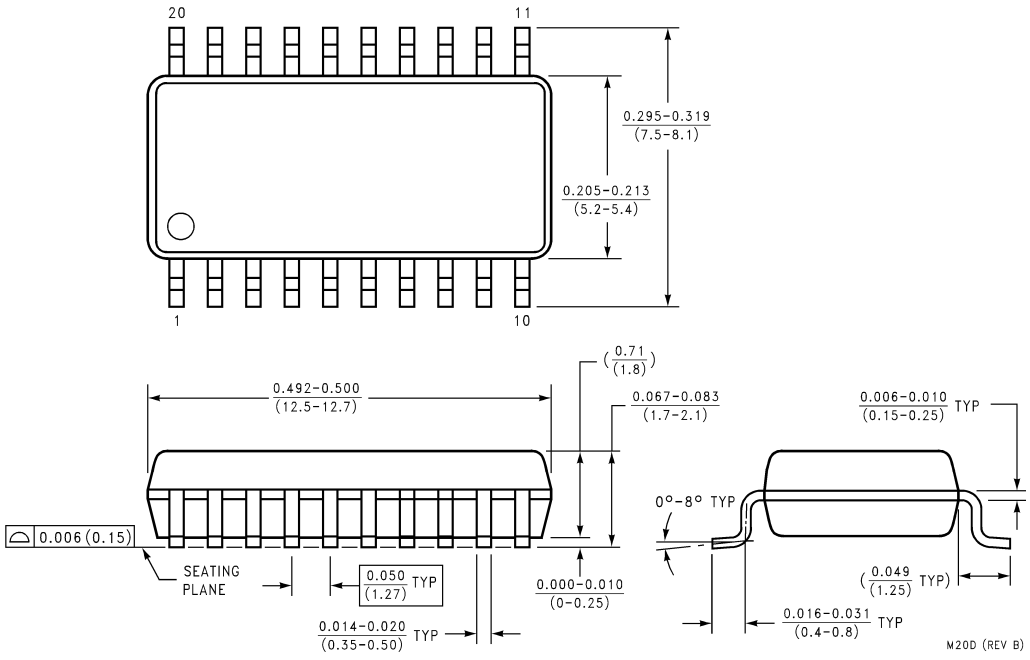
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted

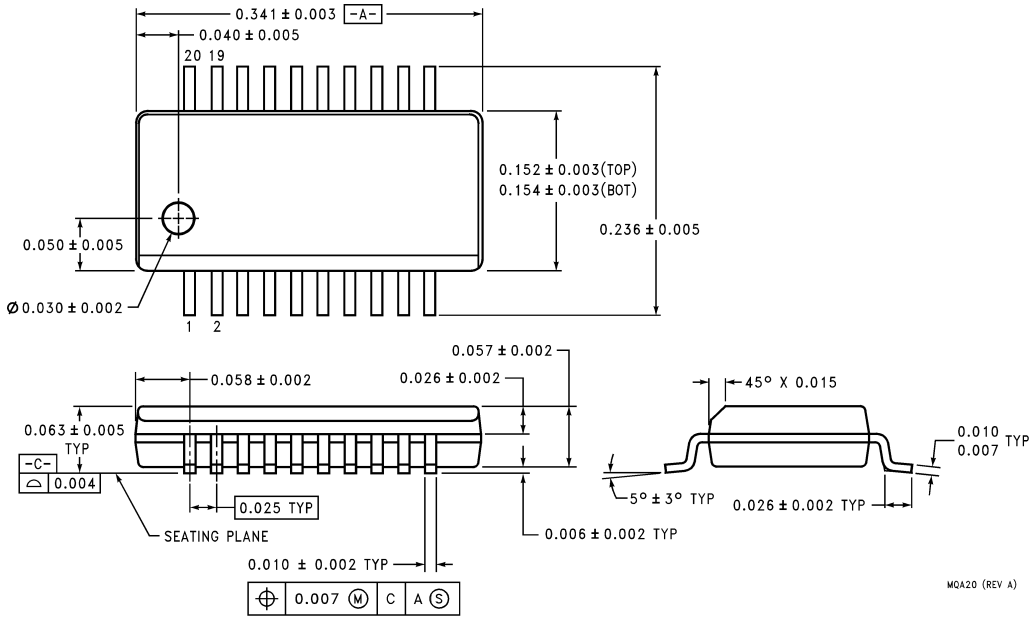


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC, EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC
(also known as QSOP)
Package Number MQA20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1998

74LVQ241
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVQ241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

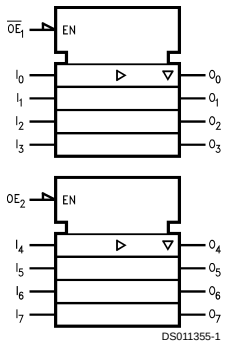
Ordering Code:

Order Number	Package Number	Package Description
74LVQ241SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ241SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
74LVQ241QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

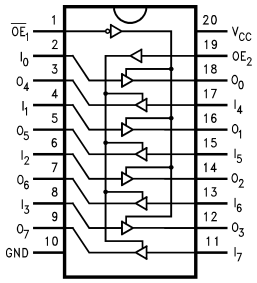
IEEE/IEC



DS011355-1

Connection Diagram

Pin Assignment for SOIC andQSOP



DS011355-2

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
OE_2	I_n	(Pins 3, 5, 7, 9)
L	X	Z
H	H	H
H	L	L

H = HIGH Voltage Level
X = Immaterial
L = LOW Voltage Level
Z = High Impedance

Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, OE_2	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings.The "Recommended Operating Conditions" table will define the conditionsfor actual device operation

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C		T_A = −40˚C to +85˚C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}	Output Current (Note 4)	3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data Inputs are driven 0V to 3.3V. One output @ GND.

Note 8: Max number of Data Inputs (n) switching. n−1 Inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.0	7.8	12.7	2.0	14.0	ns
t_{PLH}	Data to Output	3.3 ±0.3	2.0	6.5	9.0	2.0	9.5	
t_{PZL}	Output Enable Time	2.7	2.5	9.6	18.3	2.5	19.0	ns
t_{PZH}		3.3 ±0.3	2.5	8.0	13.0	2.5	13.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.2	20.4	1.0	21.0	ns
t_{PLZ}		3.3 ±0.3	1.0	8.5	14.5	1.0	15.0	
t_{OSHL}	Output to Output	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Skew Data to Output (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

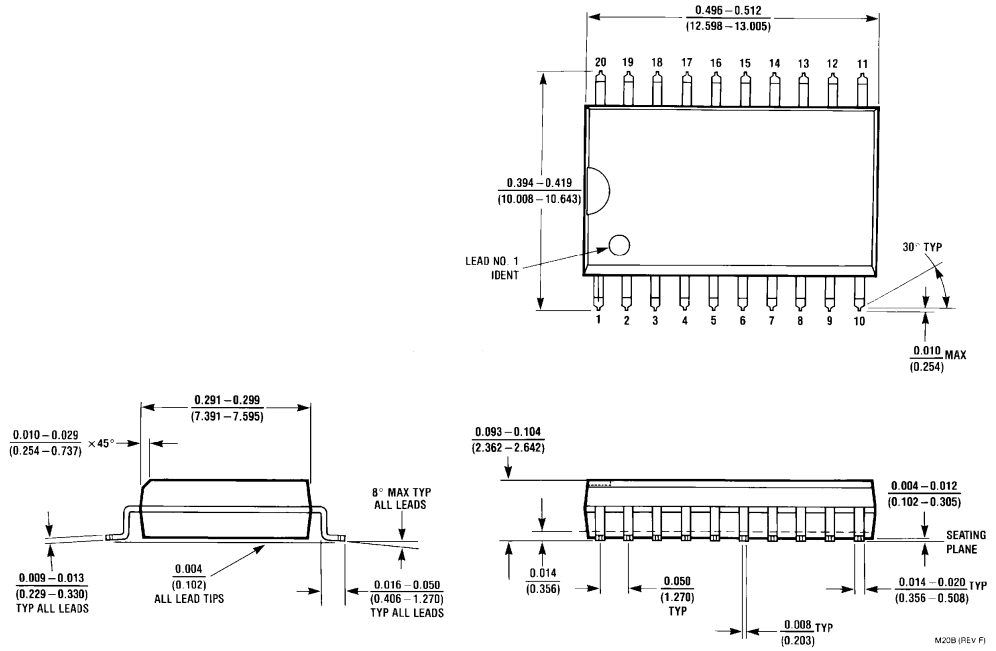
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.The specification applies to any outputs switching in the same direction,either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

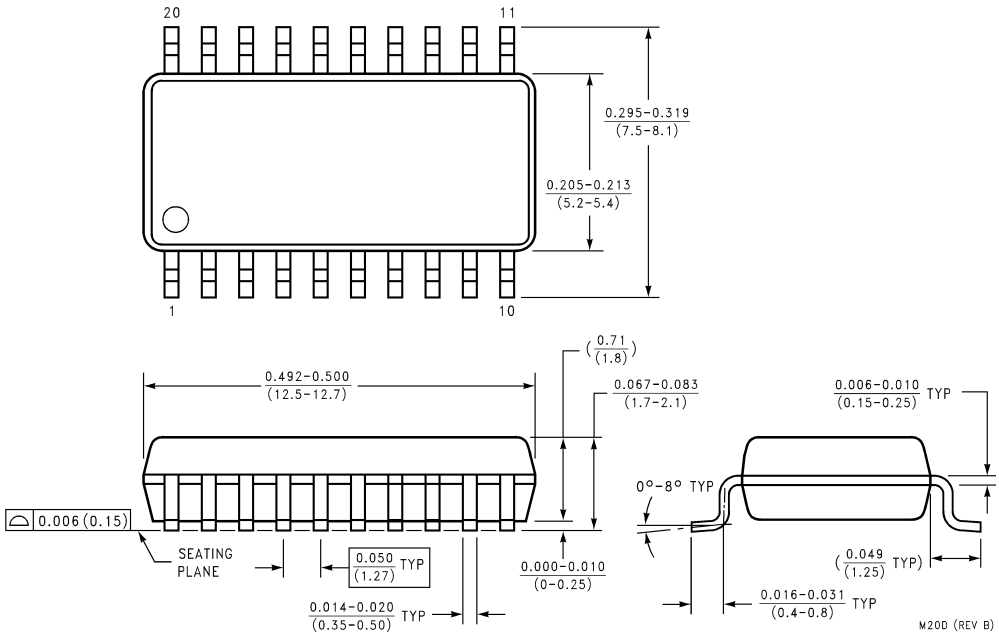
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	70	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted

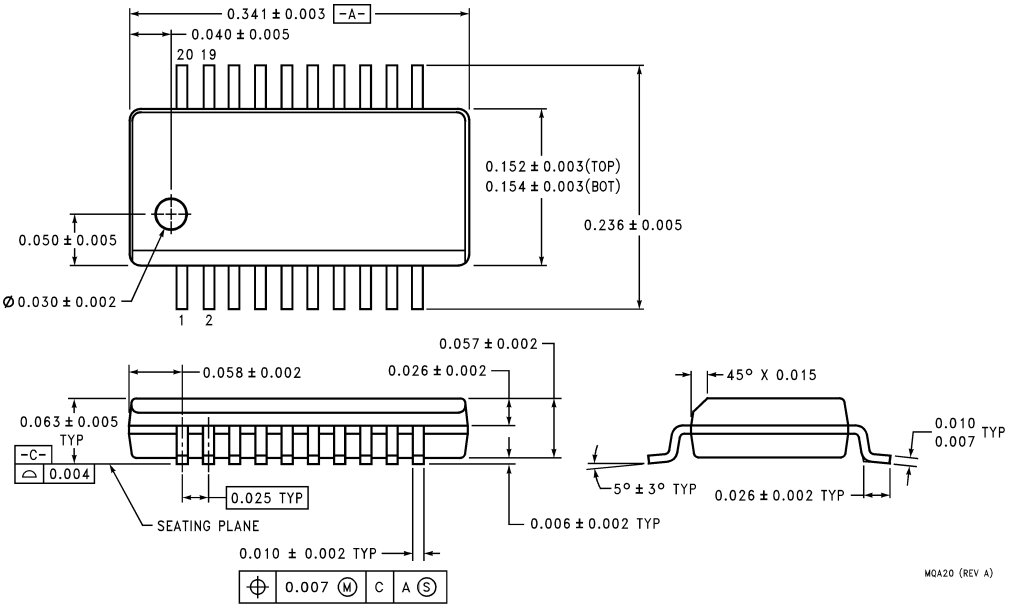


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC
(also known as QSOP)
Package Number MQA20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ244
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVQ244 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

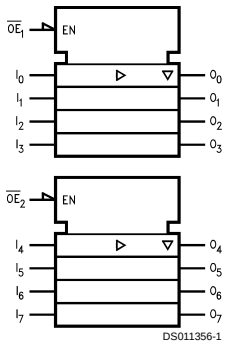
Ordering Code:

Order Number	Package Number	Package Description
74LVQ244SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
74LVQ244SJ	M20D	20-Lead Shrink Molded Small Outline Package, SOIC, EIAJ
74LVQ244QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

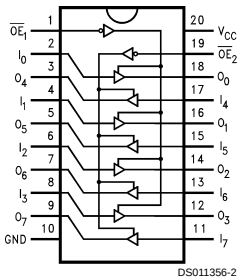
IEEE/IEC



DS011356-1

Connection Diagram

Pin Assignment for SOIC and QSOP



DS011356-2

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V_I ($\overline{OE}$) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Minimum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.7	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.0	8.4	12.7	2.0	14.0	ns
t_{PLH}	Data to Output	3.3 ±0.3	2.0	7.0	9.0	2.0	9.5	
t_{PZL}	Output Enable Time	2.7	2.5	9.6	16.9	2.5	18.0	ns
t_{PZH}		3.3 ±0.3	2.5	8.0	12.0	2.5	12.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.8	19.0	1.0	20.0	ns
t_{PLZ}		3.3 ±0.3	1.0	9.0	13.5	1.0	14.0	
t_{OSHL}	Output to Output	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Skew Data to Output (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

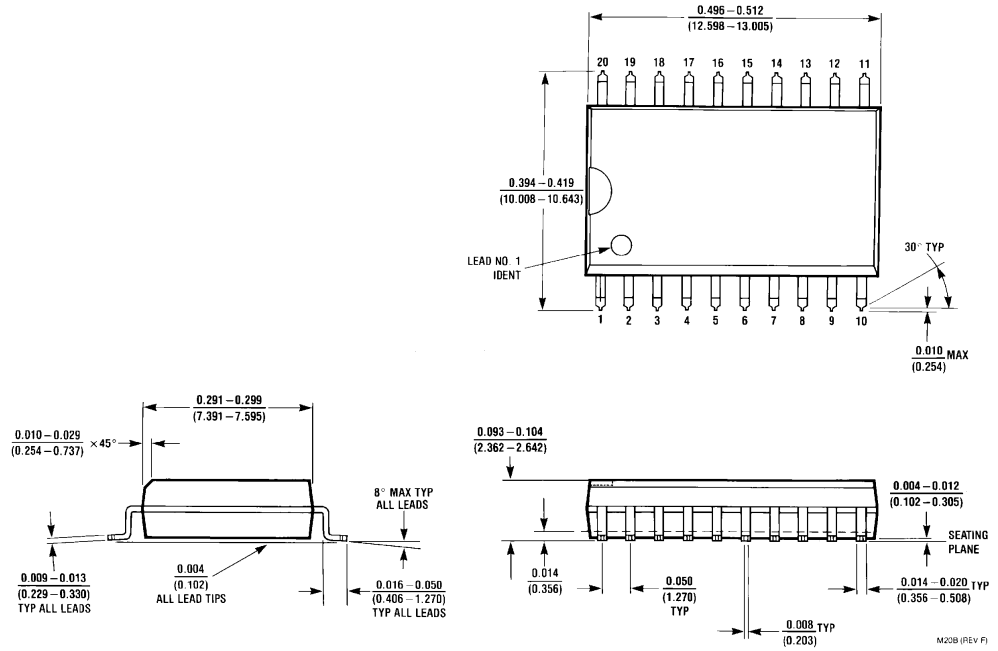
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

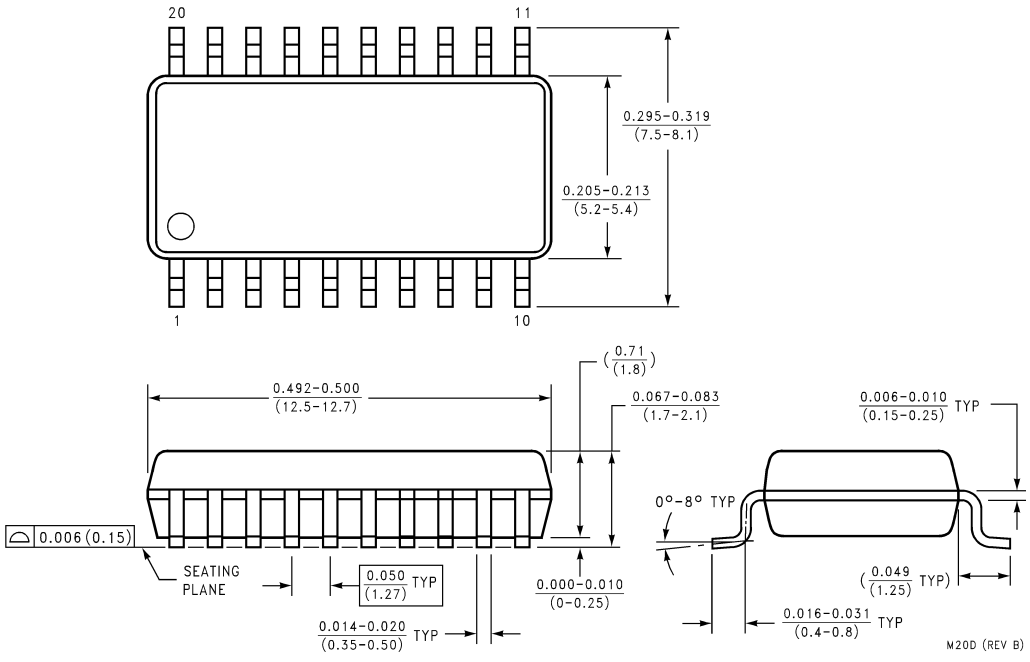
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	70	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted

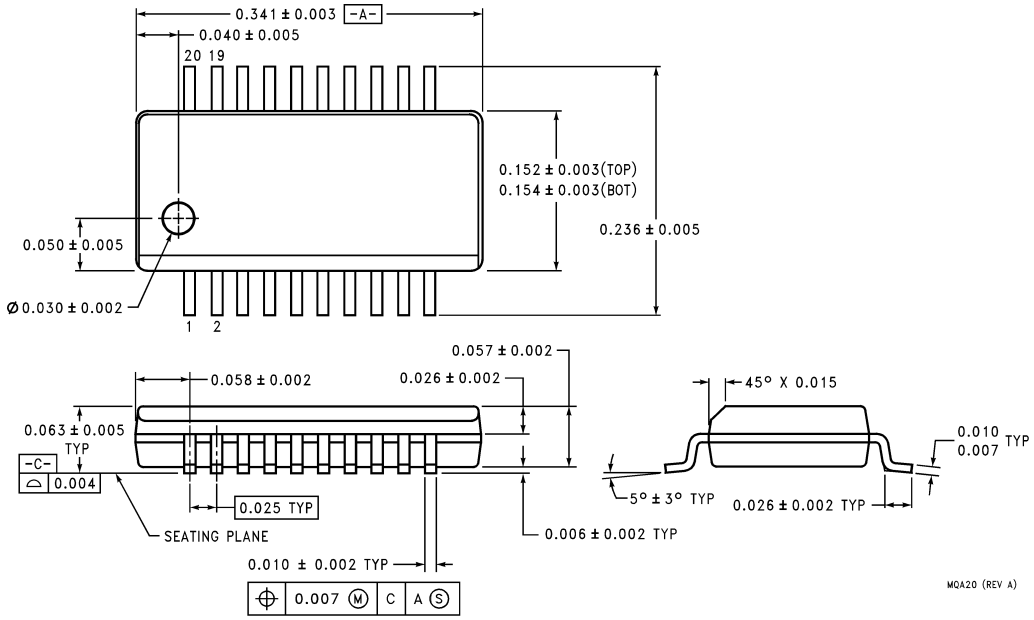


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
Package Number M20B



20-Lead Shrink Molded Small Outline Package, SOIC, EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC
(also known as QSOP)
Package Number MQA20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ245
Low Voltage Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The LVQ245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 12 mA at both the A and B ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

Features

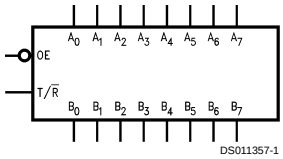
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

Ordering Code

Order Number	Package Number	Package Description
74LVQ245SC	M20B	20-Lead (0.300" Wide) Small Outline Package, SOIC JEDEC
74LVQ245SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
74LVQ245QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC

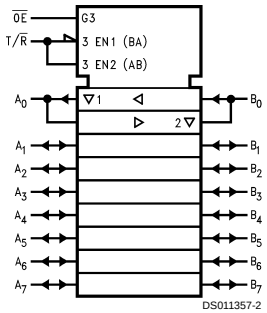
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011357-1

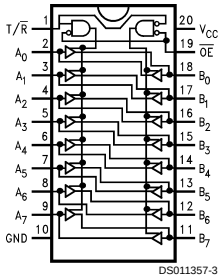
IEEE/IEC



DS011357-2

Connection Diagram

Pin Assignment for SOIC and QSOP



DS011357-3

Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Inputs
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V V_{CC} @ 3.0V	125 mV/ ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C		T_A = −40˚C to +85˚C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = +12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZT}	Maximum I/O Leakage Current	3.6		±0.3	±3.0	μA	V_I ($\overline{OE}$) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.7	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.0	9.0	14.0	2.0	15.0	ns
t_{PLH}		3.3 ±0.3	2.0	7.5	10.0	2.0	10.5	
t_{PZL}	Output Enable Time	2.7	3.0	10.2	18.3	3.0	19.0	ns
t_{PZH}		3.3 ±0.3	3.0	8.5	13.0	3.0	13.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.2	20.4	1.0	21.0	ns
t_{PLZ}		3.3 ±0.3	1.0	8.5	14.5	1.0	15.0	
t_{OSHL}	Output to Output	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Skew (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

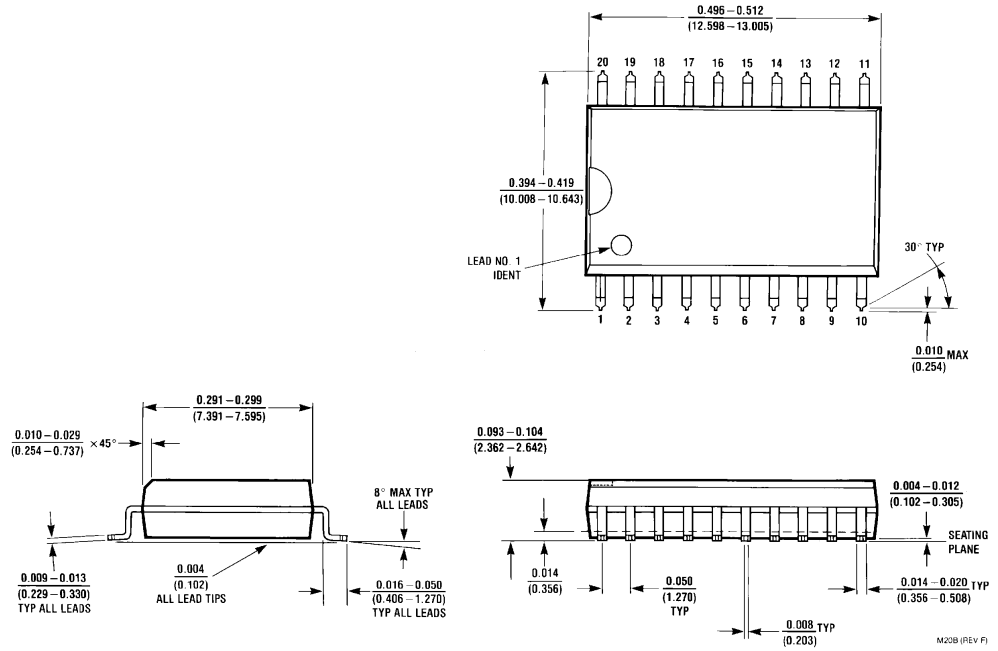
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameterguaranteed by design.

Capacitance

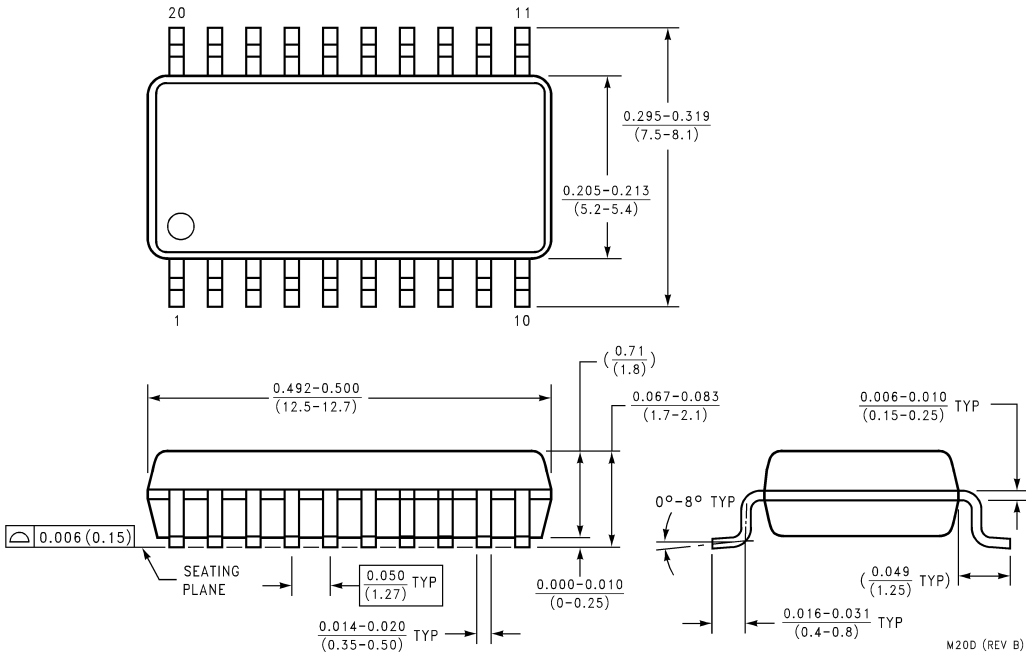
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
$C_{I/O}$	Input/Output Capacitance	15	pF	V_{CC} = 3.3V
C_{PD} (Note 10)	Power Dissipation Capacitance	67	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted

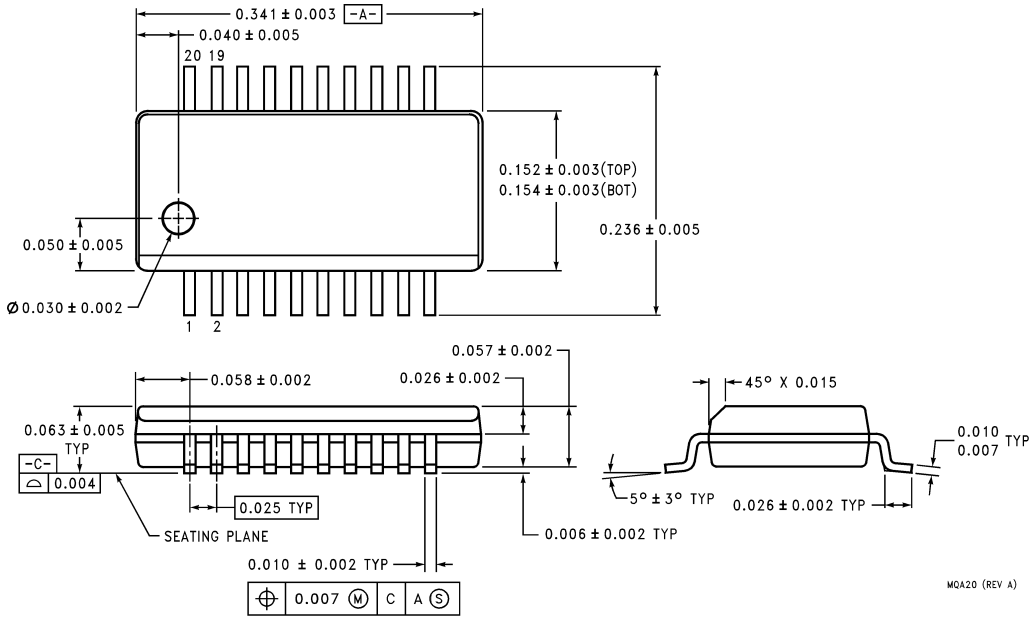


20-Lead (0.300" Wide) Small Outline Package, SOIC JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC
(also known as QSOP)
Package Number MQA20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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April 1998

74LVQ273
Low Voltage Octal D-Type Flip-Flop

General Description

The LVQ273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) input load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

Features

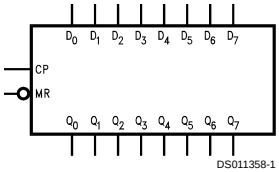
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

Ordering Code:

Order Number	Package Number	Package Description
74LVQ273SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ273SJ	M20D	20-Lead Shrink Molded Small Outline Package, SOIC EIAJ
74LVQ273QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC

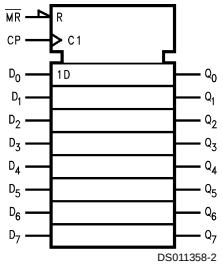
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



DS011358-1

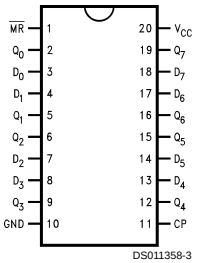
IEEE/IEC



DS011358-2

Connection Diagram

Pin Assignment for SOIC and QSOP



DS011358-3

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ΔV/Δt	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data Inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25^\circ C$, $C_L = 50$ pF			$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock	2.7	50			45		MHz
	Frequency	3.3 ±0.3	90			75		
t_{PLH}	Propagation Delay	2.7	4.0	9.6	17.6	3.0	20.0	ns
	CP to Q_n	3.3 ±0.3	4.0	8.0	12.5	3.0	14.0	
t_{PHL}	Propagation Delay	2.7	4.0	10.2	18.3	3.5	20.5	ns
	CP to Q_n	3.3 ±0.3	4.0	8.5	13.0	3.5	14.5	
t_{PHL}	Propagation Delay	2.7	4.0	10.2	18.3	3.5	20.0	ns
	$\overline{MR}$ to Q_n	3.3 ±0.3	4.0	8.5	13.0	3.5	14.0	
t_{OSHL}	Output to Output	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Skew (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

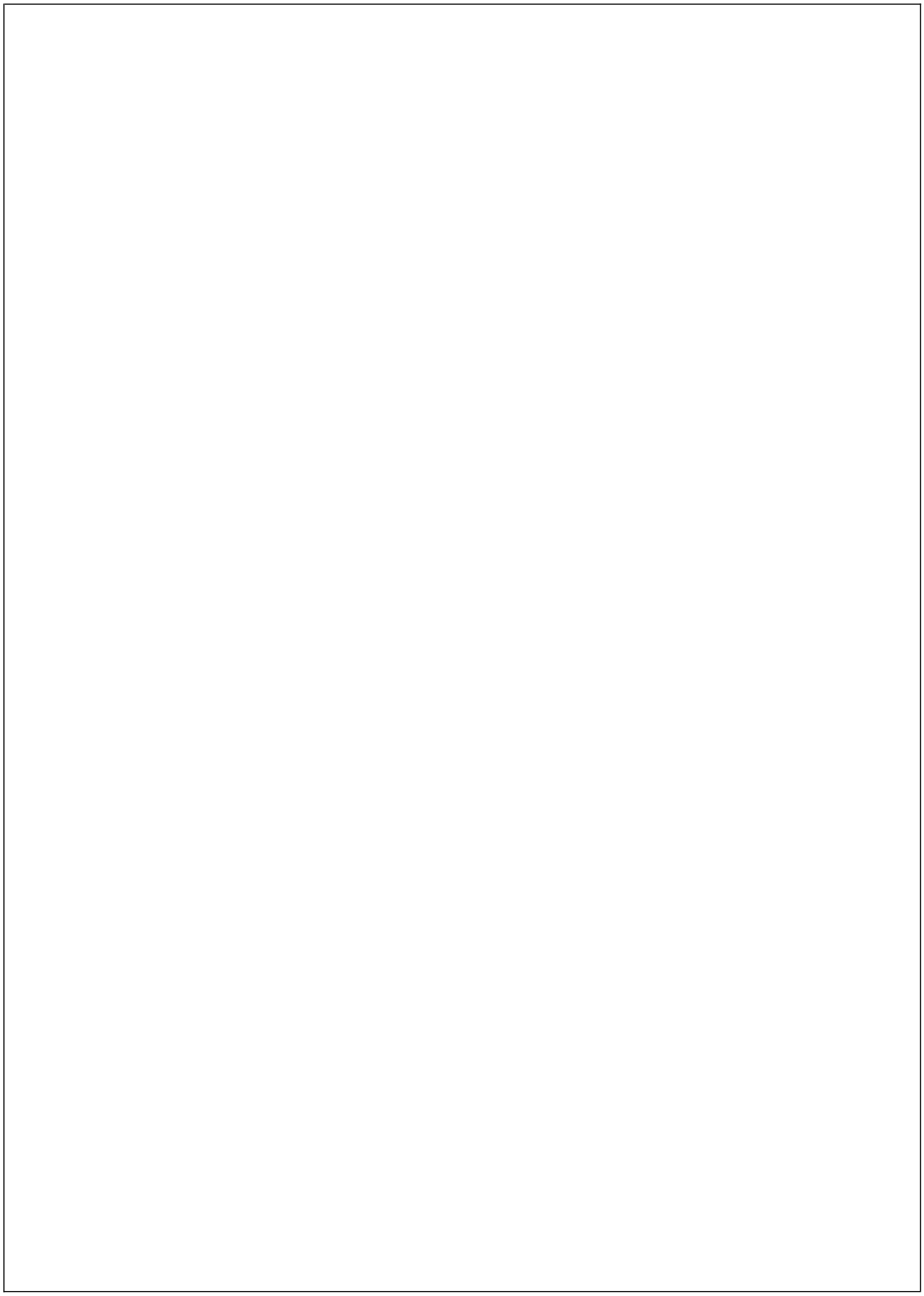
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = +25^\circ C$, $C_L = 50$ pF		$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	2.7		6.5	8.5	ns
	D_n to CP	3.3 ±0.3		5.0	6.0	
t_H	Hold Time, HIGH or LOW	2.7		0.0	0.0	ns
	D_n to CP	3.3 ±0.3		0.0	0.0	
t_W	Clock Pulse Width	2.7		7.0	8.5	ns
	HIGH or LOW	3.3 ±0.3		5.5	6.0	
t_W	$\overline{MR}$ Pulse Width	2.7		7.0	8.5	ns
	HIGH or LOW	3.3 ±0.3		5.5	6.0	
t_W	Recovery Time	2.7		5.0	6.5	ns
	$\overline{MR}$ to CP	3.3 ±0.3		4.0	4.5	

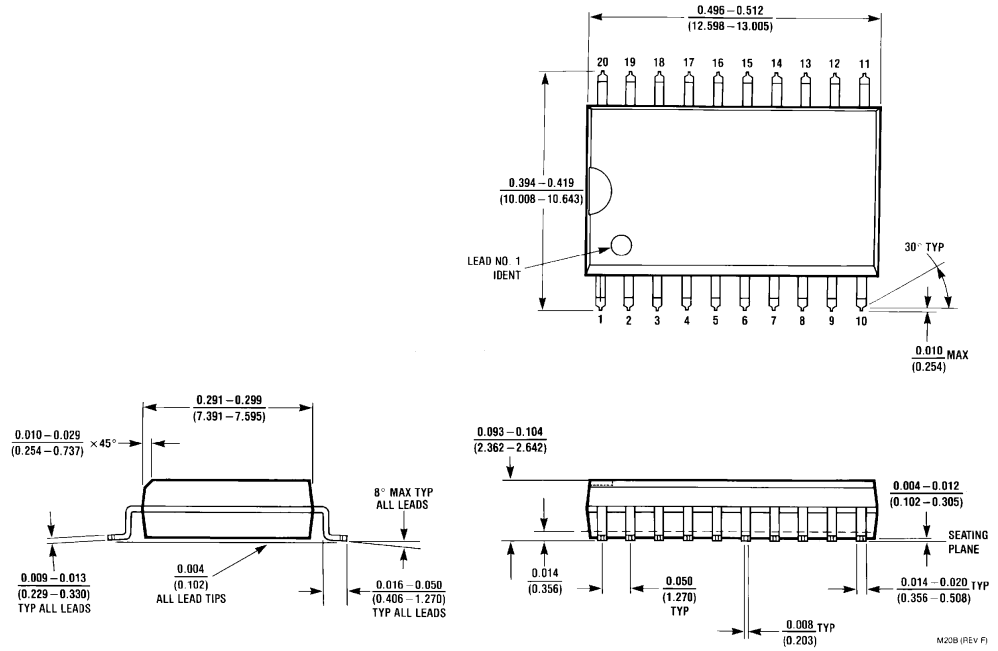
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	35	pF	V_{CC} = 3.3V

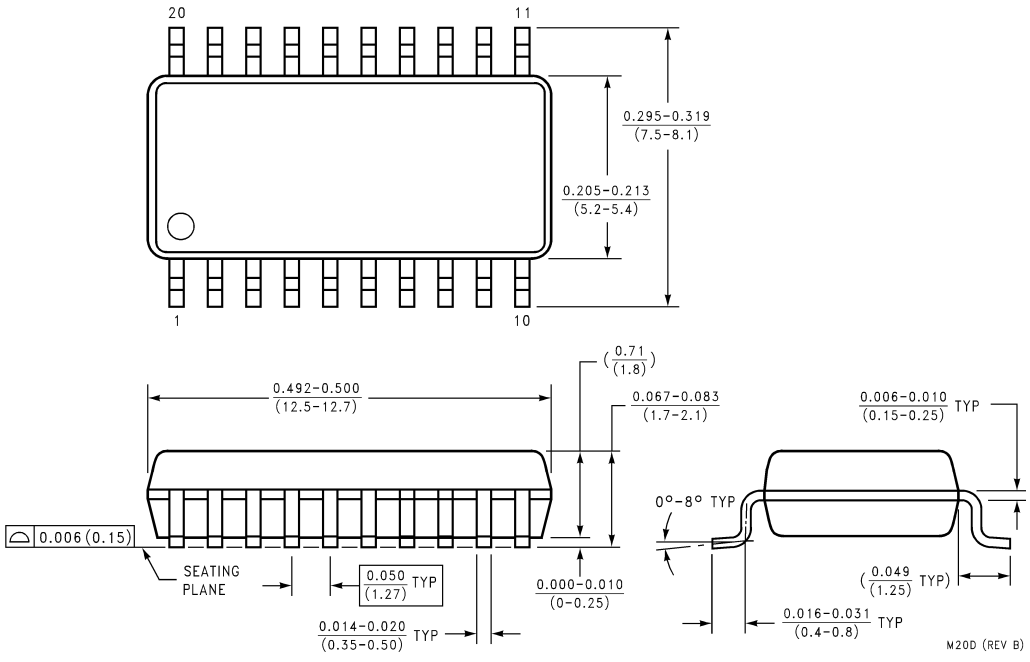
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted

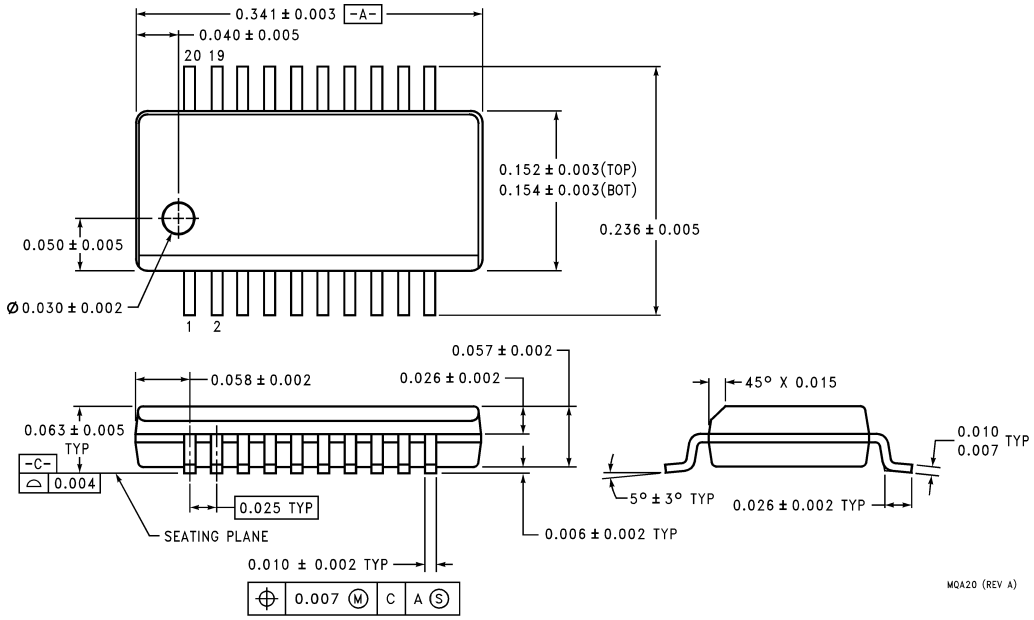


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
Package Number M20B



20-Lead Shrink Molded Small Outline Package, SOIC EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC
(also known as QSOP)
Package Number MQA20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ32
Low Voltage Quad 2-Input OR Gate

General Description

The LVQ32 contains four 2-input OR gates.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

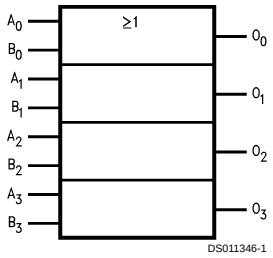
Ordering Code:

Order Number	Package Number	Package Description
74LVQ32SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
74LVQ32SJ	M14D	14-Lead Molded Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

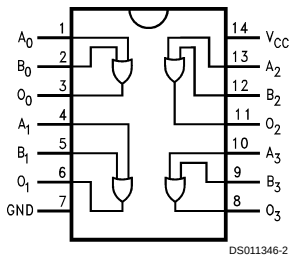
IEEE/IEC



DS011346-1

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011346-2

Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	
LVQ	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74LVQ	−40°C to +85°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	µA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.9	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.8	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

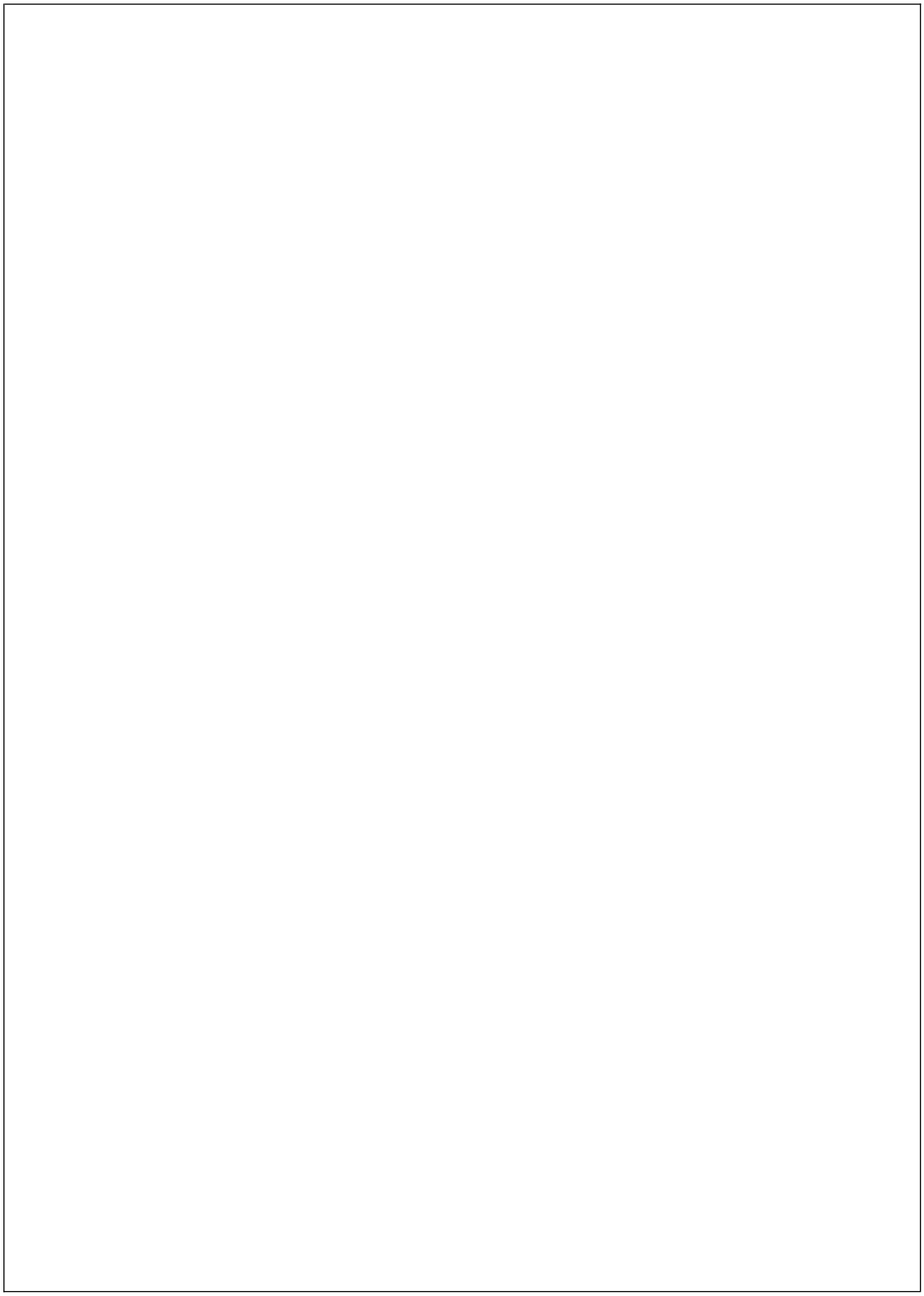
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	1.5	8.4	12.7	1.5	14.0	ns
		3.3 ±0.3	1.5	7.0	9.0	1.5	10.0	
t_{PHL}	Propagation Delay	2.7	1.5	8.4	12.0	1.0	13.0	ns
		3.3 ±0.3	1.5	7.0	8.5	1.5	9.0	
$t_{OSHL,}$	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	(Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

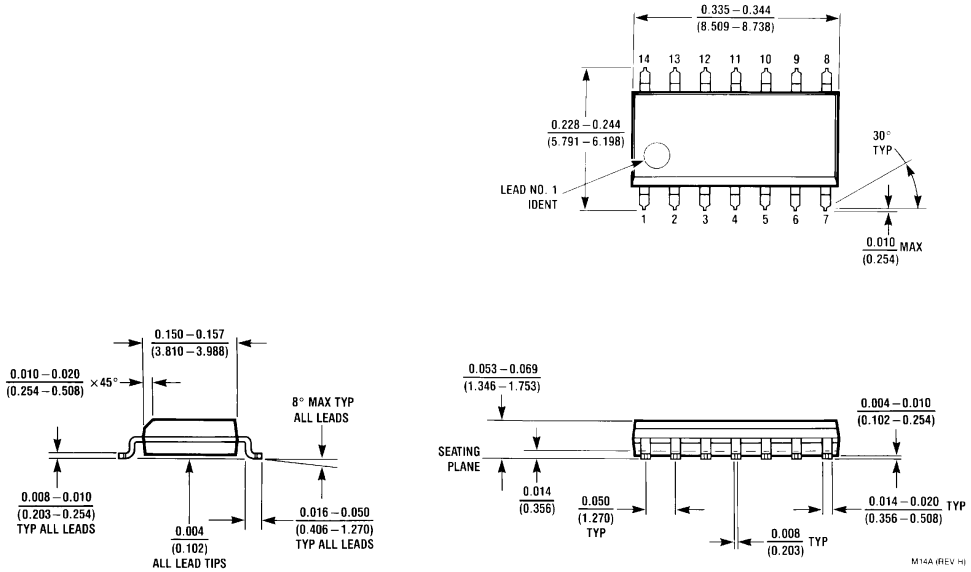
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	17	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

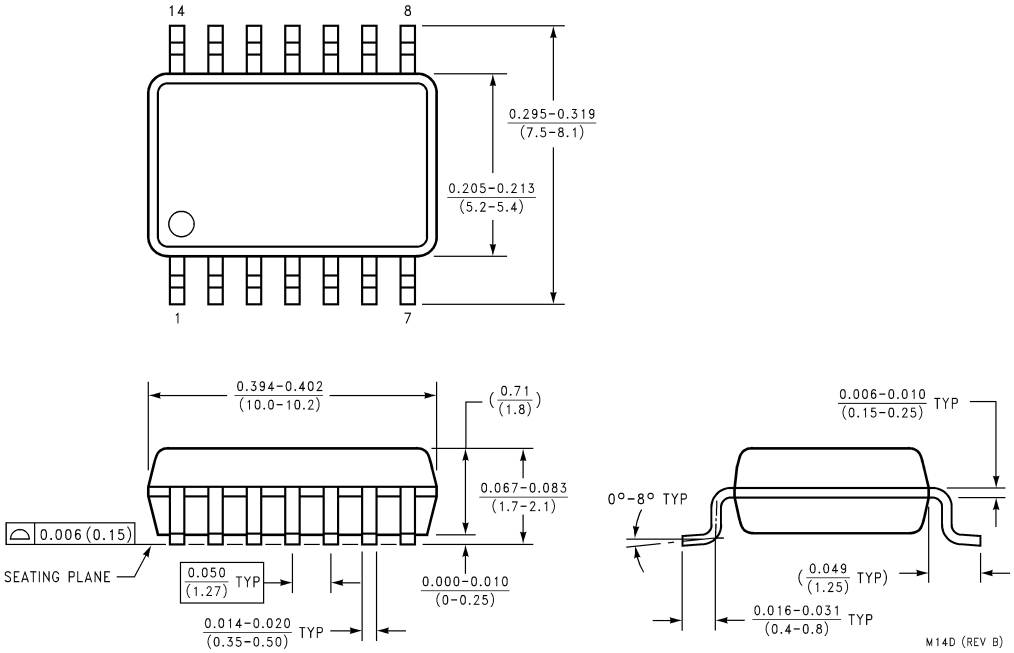


Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded Small Outline Package, SOIC EIAJ
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ373
Low Voltage Octal Transparent Latch with 3-STATE Outputs

General Description

The LVQ373 consists of eight latches with 3-STATE outputs for bus organized system applications. The latches appear transparent to the data when Latch Enable (LE) is HIGH. When LE is low, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state.

Features

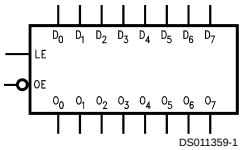
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

Ordering Code:

Order Number	Package Number	Package Description
74LVQ373SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ373SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
74LVQ373QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC

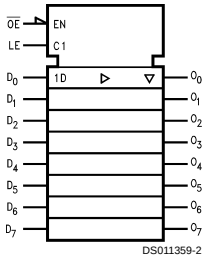
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



DS011359-1

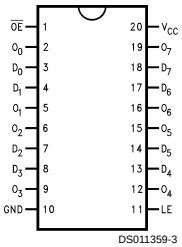
IEEE/IEC



DS011359-2

Connection Diagram

Pin Assignment for SOIC and QSOP



DS011359-3

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Functional Description

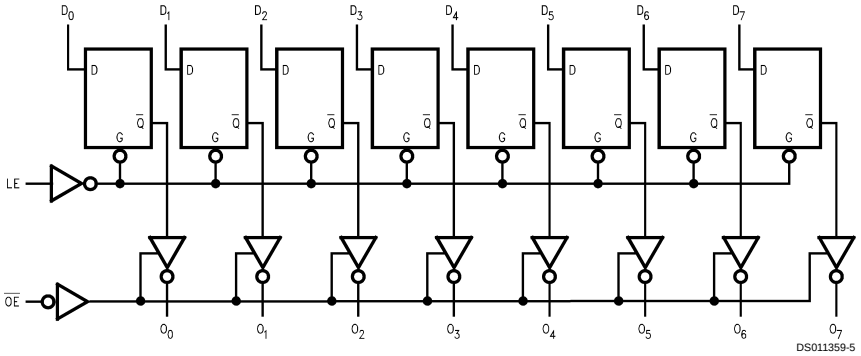
The LVQ373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW, the latches store the information that was present on the D-type inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH to Low transition of Latch Enable

Logic Diagram



DS011359-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Inused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.5	9.6	14.8	2.5	16.0	ns
t_{PLH}	D_n to O_n	3.3 ±0.3	2.5	8.0	10.5	2.5	11.0	
t_{PLH}	Propagation Delay	2.7	2.5	9.6	16.9	2.5	18.0	n
t_{PHL}	LE to O_n	3.3 ±0.3	2.5	8.0	12.0	2.5	12.5	
t_{PZL}	Output Enable Time	2.7	2.5	10.2	18.3	2.5	19.0	ns
t_{PZH}		3.3 ±0.3	2.5	8.5	13.0	2.5	13.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.8	20.4	1.0	21.0	ns
t_{PLZ}		3.3 ±0.3	1.0	9.0	14.5	1.0	15.0	
t_{OSHL}	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	(Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

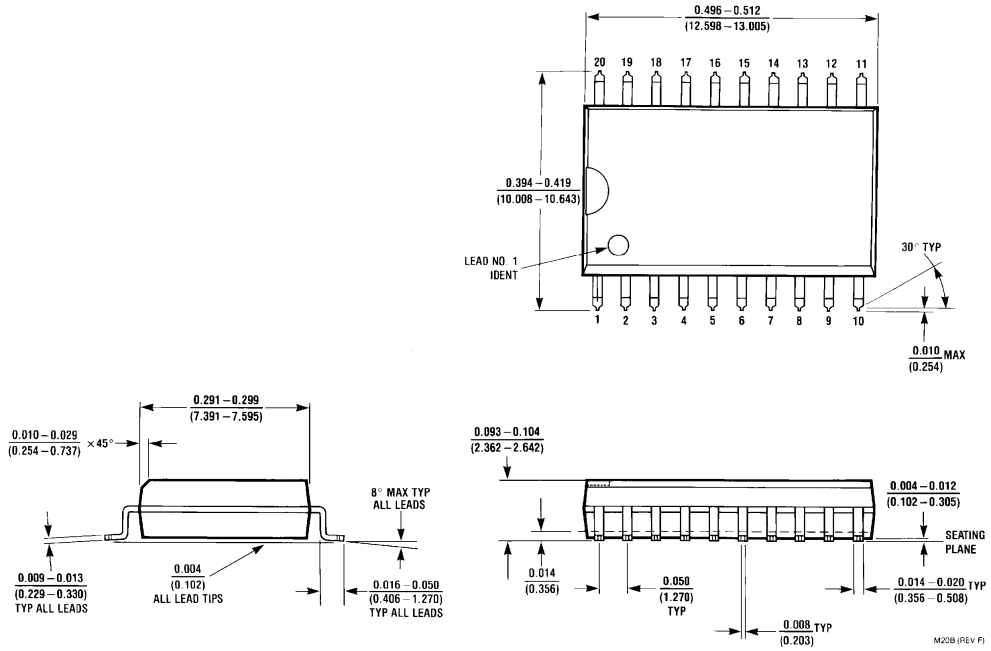
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF		T_A = −40°C to +85°C, C_L = 50 pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	2.7	0	4.0	4.5	ns
		3.3 ±0.3	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	2.7	0	1.5	1.5	ns
		3.3 ±0.3	0	1.5	1.5	
t_W	LE Pulse Width, HIGH	2.7	2.4	5.0	6.0	ns
		3.3 ±0.3	2.0	4.0	4.0	

Capacitance

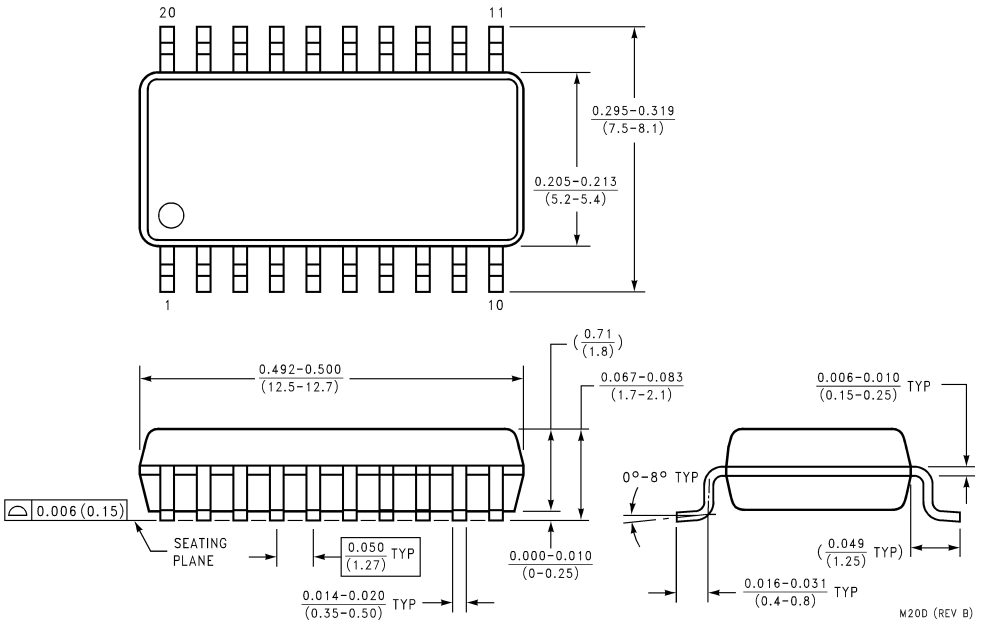
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	39	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted

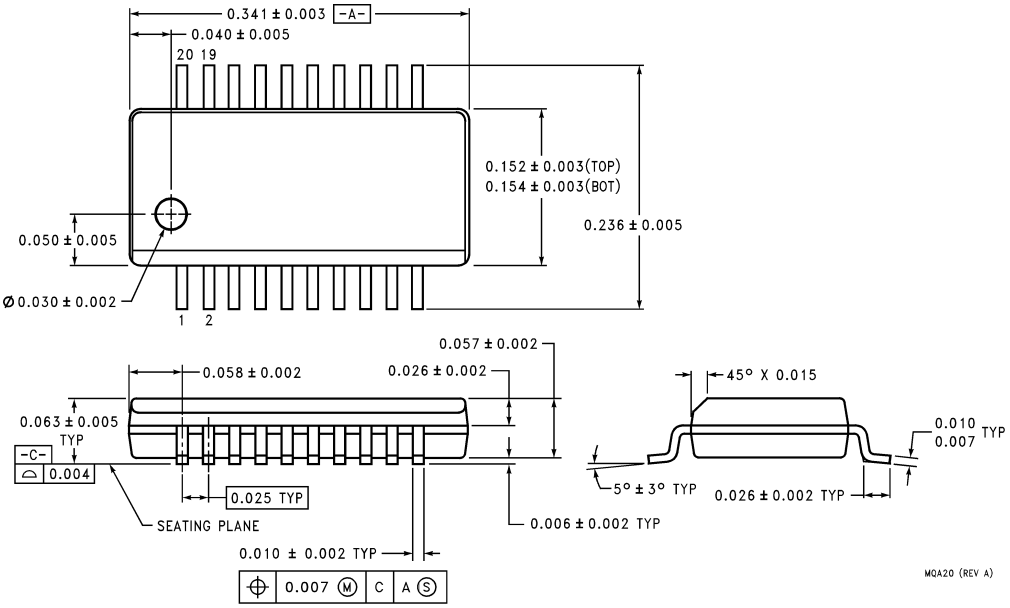


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP JEDEC
(also known as QSOP)
Package Number MQA20

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FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ374
Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVQ374 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

Features

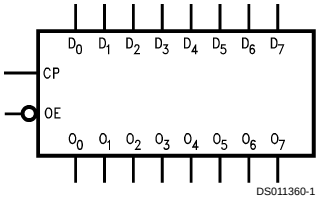
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity
- Buffered positive edge-triggered clock
- 3-STATE outputs drive bus lines or buffer memory address registers

Ordering Code:

Order Number	Package Number	Package Description
74LVQ374SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ374SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
74LVQ374QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SOIC JEDEC

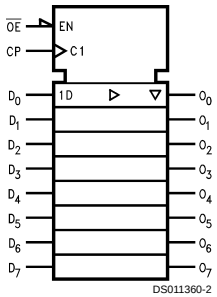
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011360-1

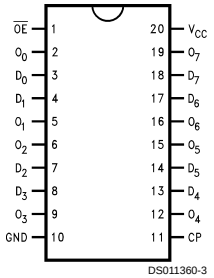
IEEE/IEC



DS011360-2

Connection Diagram

Pin Assignment for SOIC and QSOP



DS011360-3

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

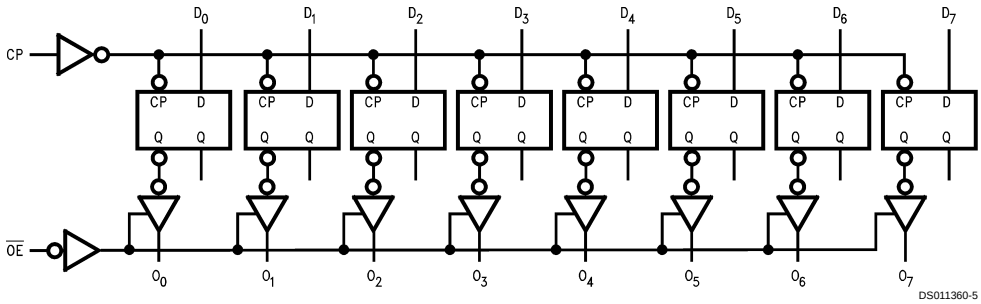
Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Functional Description

The LVQ374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



DS011360-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C		T_A = −40˚C to +85˚C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 µA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 µA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	µA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	µA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock Frequency	2.7	55			50		MHz
		3.3 ±0.3	75			70		
t_{PLH}	Propagation Delay	2.7	3.0	11.4	18.3	3.0	19.0	ns
t_{PHL}	CP to O_n	3.3 ±0.3	3.0	9.5	13.0	3.0	13.5	
t_{PZL}	Output Enable Time	2.7	3.0	11.4	18.3	3.0	19.0	ns
t_{PZH}		3.3 ±0.3	3.0	9.5	13.0	3.0	13.5	
t_{PHZ}	Output Disable Time	2.7	1.0	11.4	20.4	1.0	21.0	ns
t_{PLZ}		3.3 ±0.3	1.0	9.5	14.5	1.0	15.0	
t_{OSHL}	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	CP to O_n	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

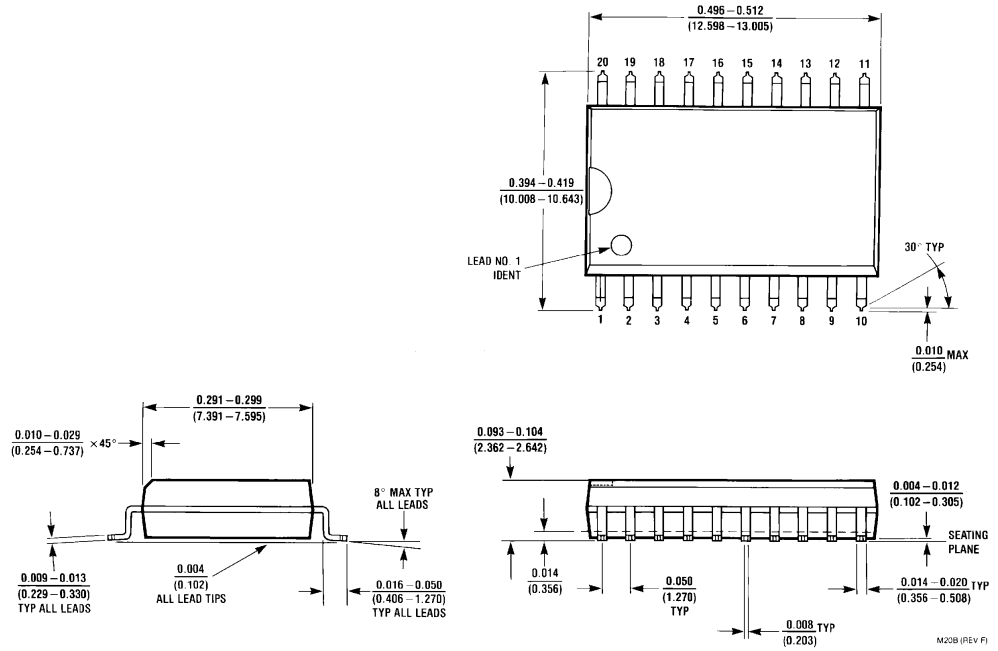
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF		T_A = 40°C− to +85°C, C_L = 50 pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	2.7	0	4.0	4.5	ns
	D_n to CP	3.3 ±0.3	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	2.7	0	1.5	1.5	ns
	D_n to CP	3.3 ±0.3	0	1.5	1.5	
t_W	CP Pulse Width,	2.7	2.4	5.0	6.0	ns
	HIGH or LOW	3.3 ±0.3	2.0	4.0	4.0	

Capacitance

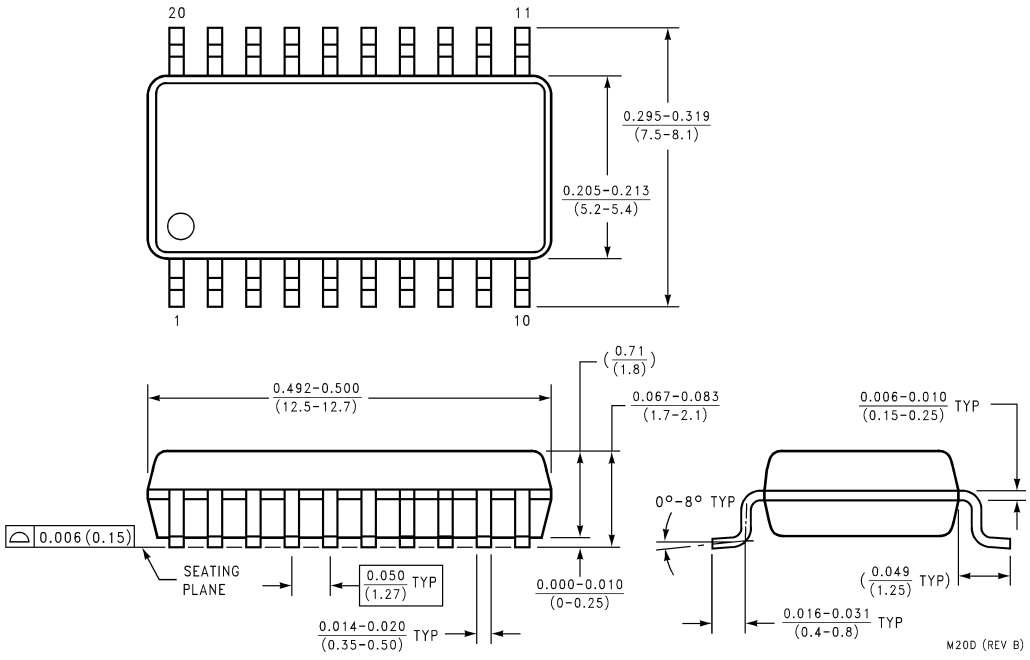
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	39	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted

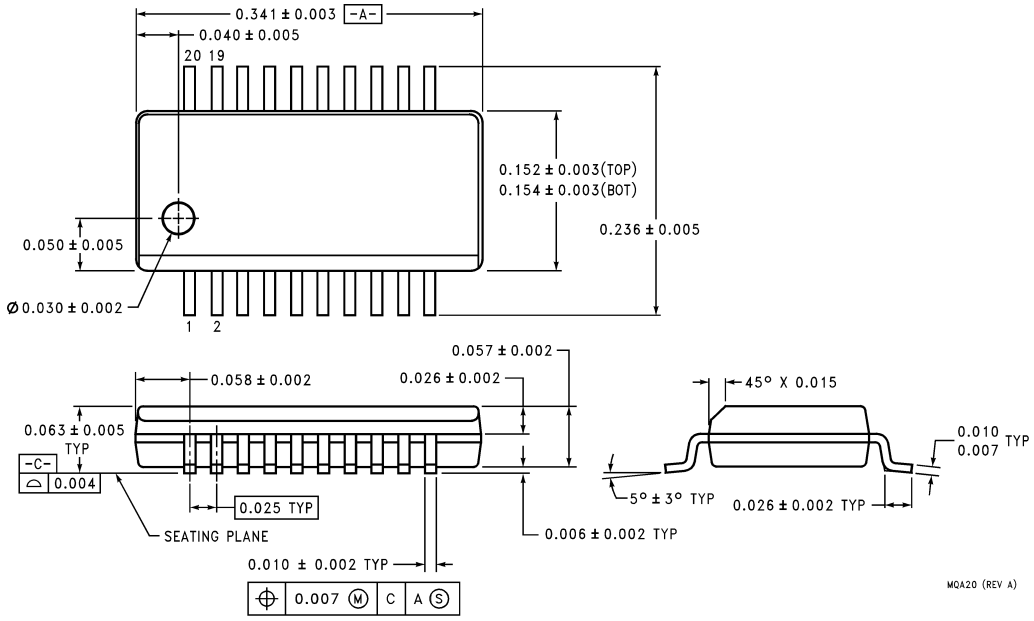


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SOIC JEDEC
(also known as QSOP)
Package Number MQA20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR TM

May 1998

74LVQ573
Low Voltage Octal Latch with 3-STATE Outputs

General Description

The LVQ573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs. The LVQ573 is functionally identical to the LVQ373 but with inputs and outputs on opposite sides of the package.

Features

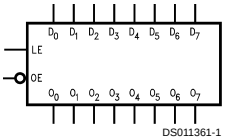
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ, and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

Ordering Code:

Order Number	Package Number	Package Description
74LVQ573SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
74LVQ573SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC, EIAJ
74LVQ573QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC

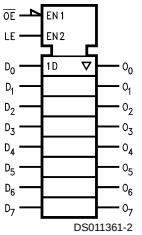
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



DS011361-1

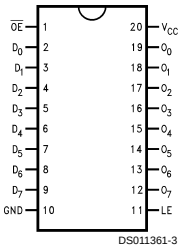
IEEE/IEC



DS011361-2

Connection Diagram

Pin Assignment for SOIC and QSOP



DS011361-3

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Truth Table

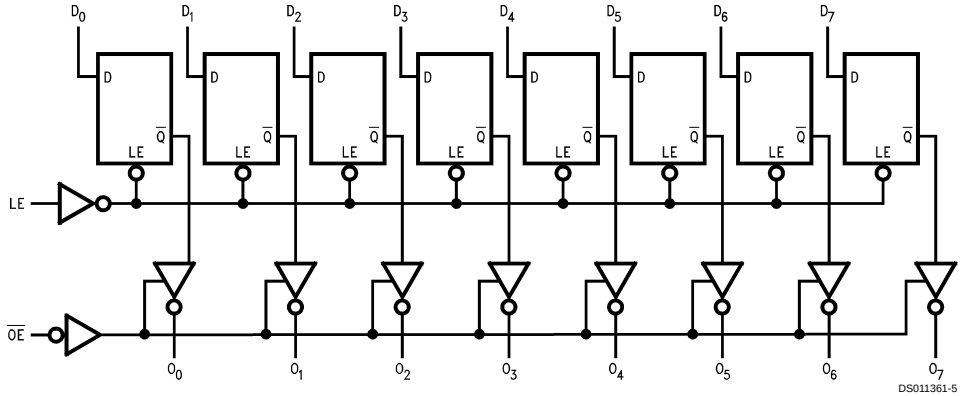
Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage
L = LOW Voltage
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Functional Description

The LVQ573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW the latches store the information that was present on the D-type inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



DS011361-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8 V_{Max} (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V V_{Min} (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	3-STATE Leakage Curent	3.6		±0.25	±2.5	μA	V_I ($\overline{OE}$) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.5	10.2	14.8	2.5	16.0	ns
t_{PLH}	D_n to O_n	3.3 ±0.3	2.5	8.5	10.5	2.5	11.0	
t_{PLH}	Propagation Delay	2.7	2.5	10.2	16.9	2.5	18.0	ns
t_{PHL}	LE to O_n	3.3 ±0.3	2.5	8.5	12.0	2.5	12.5	
t_{PZL}	Output Enable Time	2.7	2.5	10.2	18.3	2.5	19.0	ns
t_{PZH}		3.3 ±0.3	2.5	8.5	13.0	2.5	13.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.8	20.4	1.0	21.0	ns
t_{PLZ}		3.3 ±0.3	1.0	9.0	14.5	1.0	15.0	
t_{OSHL}	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	D_n to O_n	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

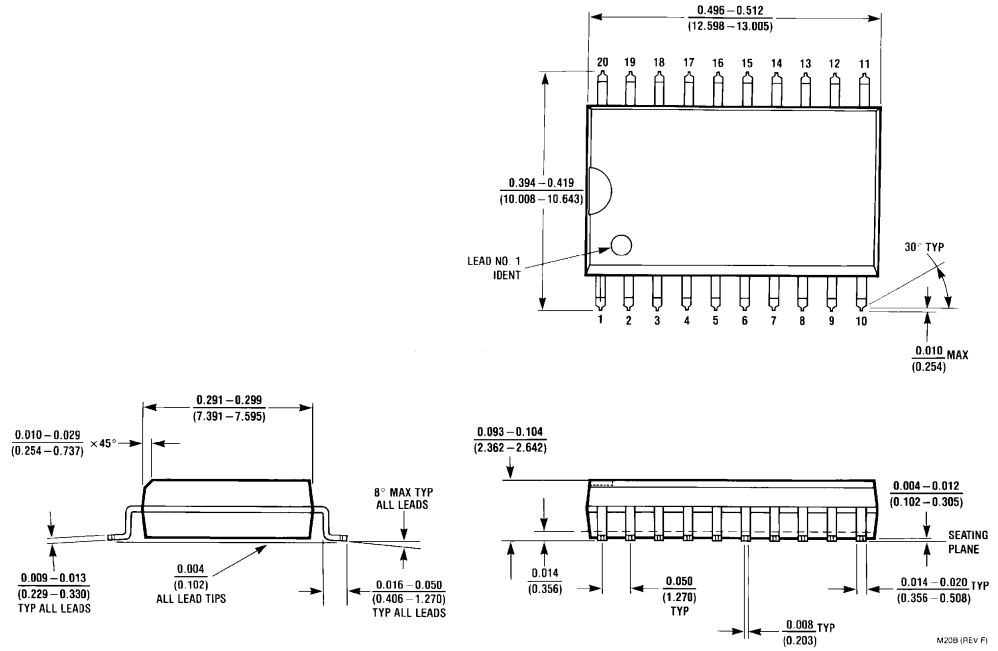
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF		T_A = −40°C to +85°C, C_L = 50 pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time, HIGH or LOW	2.7	0	4.0	4.5	ns
	D_n to LE	3.3 ±0.3	0	3.0	3.0	
t_H	Hold Time, HIGH or LOW	2.7	0	1.5	1.5	ns
	D_n to LE	3.3 ±0.3	0	1.5	1.5	
t_W	LE Pulse Width, HIGH	2.7	2.4	5.0	6.0	ns
		3.3 ±0.3	2.0	4.0	4.0	

Capacitance

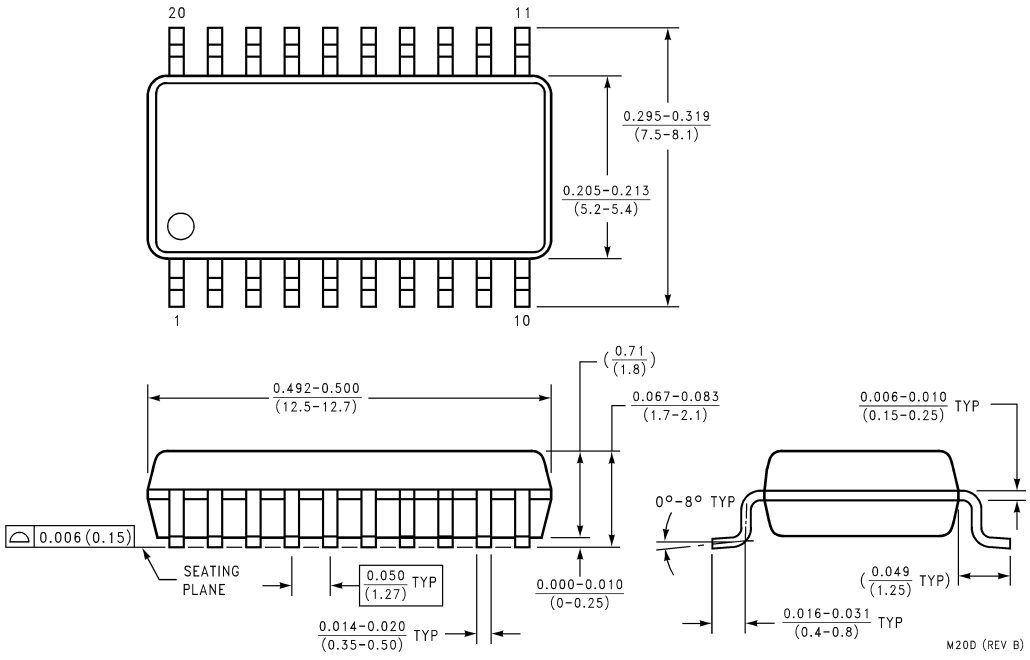
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	37	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted

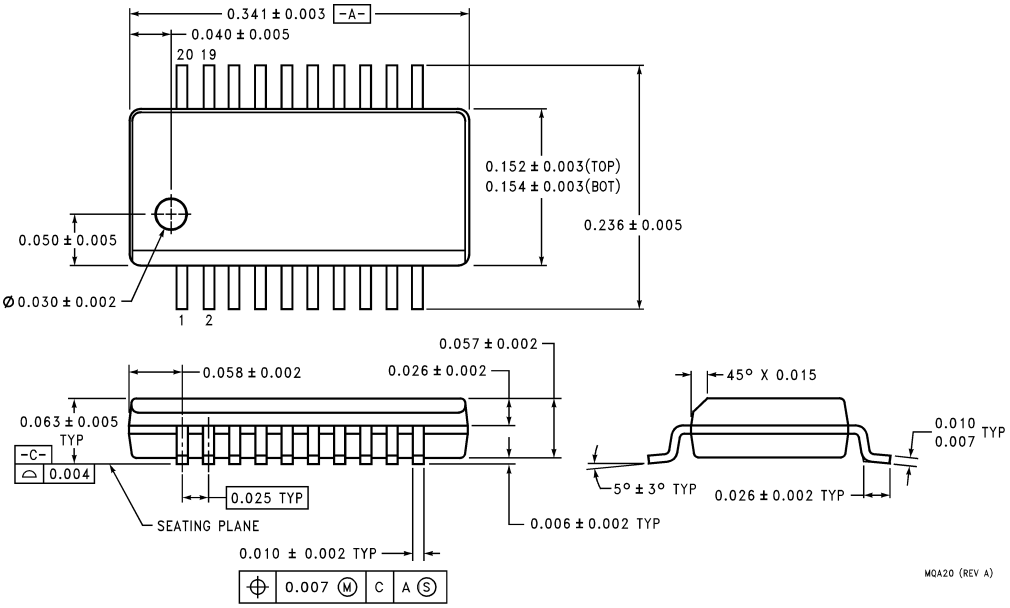


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC, EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC
(also known as QSOP)
Package Number MQA20

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May 1998

74LVQ74
Low Voltage Dual D-Type Positive Edge-Triggered Flip-Flop

General Description

The LVQ74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. Clock triggering occurs at a voltage level of the clock pulse and is not directly related to the transition time of the positive-going pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

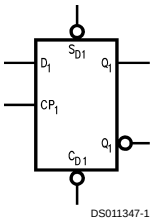
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

Ordering Code:

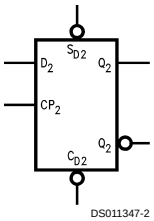
Order Number	Package Number	Package Description
74LVQ74SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, SOIC JEDEC
74LVQ74SJ	M14D	14-Lead Molded Small Outline Package, SOIC EIAJ

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols

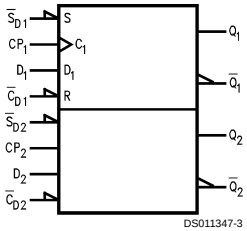


DS011347-1



DS011347-2

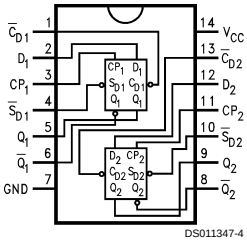
IEEE/IEC



DS011347-3

Connection Diagram

Pin Assignment for SOIC JEDEC and EIAJ



DS011347-4

Pin Descriptions

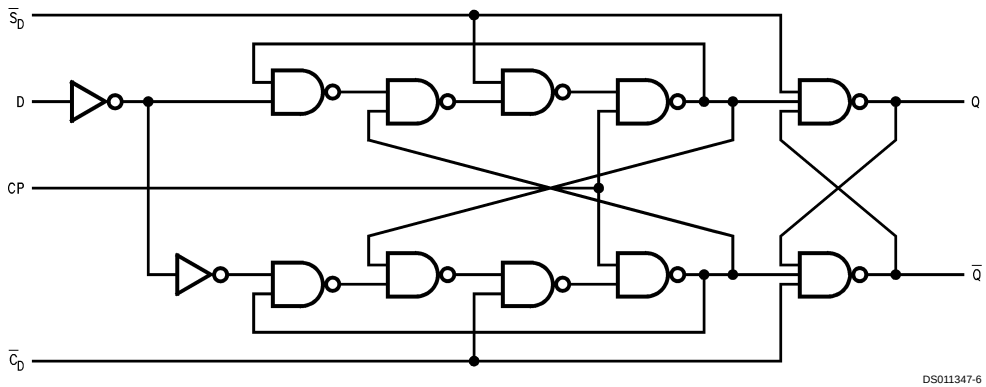
Pin Names	Description
D_1, D_2	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

Truth Table

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	⌐	H	H	L
H	H	⌐	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
$Q_0(\overline{Q}_0)$ = Previous $Q(\overline{Q})$ before LOW-to-HIGH Transition of Clock

Logic Diagram



DS011347-6

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteritics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C		T_A = −40˚C to +85˚C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4) Output Current	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.2	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.2	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.7	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock	2.7	50	100		40		MHz
	Frequency	3.3 ±0.3	100	125		95		
t_{PLH}	Propagation Delay	2.7	3.5	9.6	16.9	3.5	19.0	ns
	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n	3.3 ± 0.3	3.5	8.0	12.0	2.5	13.0	
t_{PHL}	Propagation Delay	2.7	4.0	12.6	16.9	3.5	19.0	ns
	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n	3.3 ±0.3	4.0	10.5	12.0	3.5	13.5	
t_{PLH}	Propagation Delay	2.7	4.5	9.6	19.0	4.0	23.0	ns
	CP_n to Q_n or $\overline{Q}_n$	3.3 ±0.3	4.5	8.0	13.5	4.0	16.0	
t_{PHL}	Propagation Delay	2.7	3.5	9.6	19.7	3.5	21.0	ns
	CP_n to Q_n or $\overline{Q}_n$	3.3 ±0.3	3.5	8.0	14.0	3.5	14.5	
t_{OSHL}	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Operating Requirements

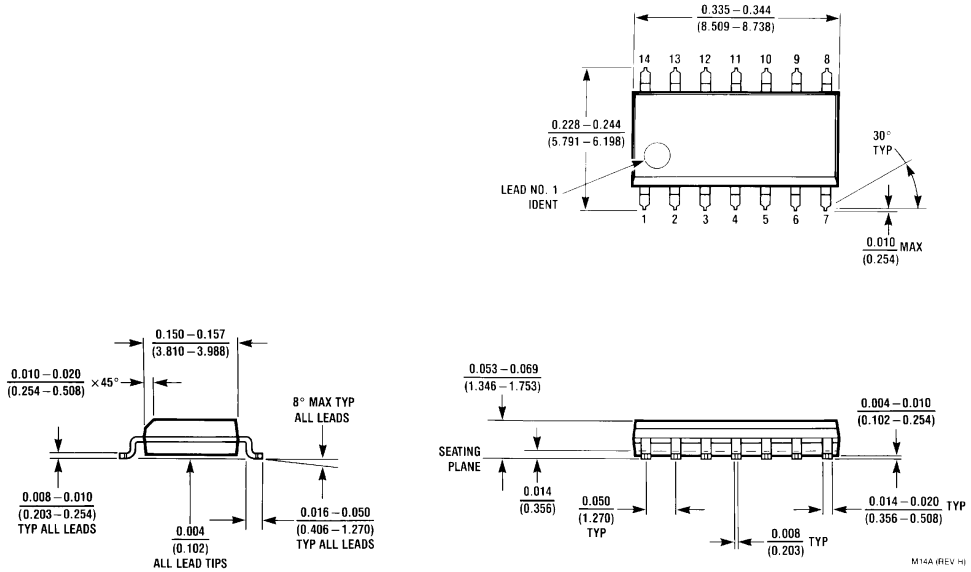
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF		T_A = −40°C to +85°C, C_L = 50 pF	Units
			Typ	Guaranteed Minimum		
t_S	Set-up Time, HIGH or LOW	2.7	1.8	5.0	6.5	ns
		3.3 ±0.3	1.5	4.0	4.5	
t_H	Hold Time, HIGH or LOW	2.7	−2.4	0.5	0.5	ns
	D_n to CP_n	3.3 ±0.3	−2.0	0.5	0.5	
t_W	Pulse Width	2.7	3.6	7.0	10.0	ns
		3.3 ±0.3	3.0	5.5	7.0	
t_{rec}	Recovery Time	2.7	−3.0	0	0	ns
		3.3 ±0.3	−2.5	0	0	

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	25	pF	V_{CC} = 3.3V

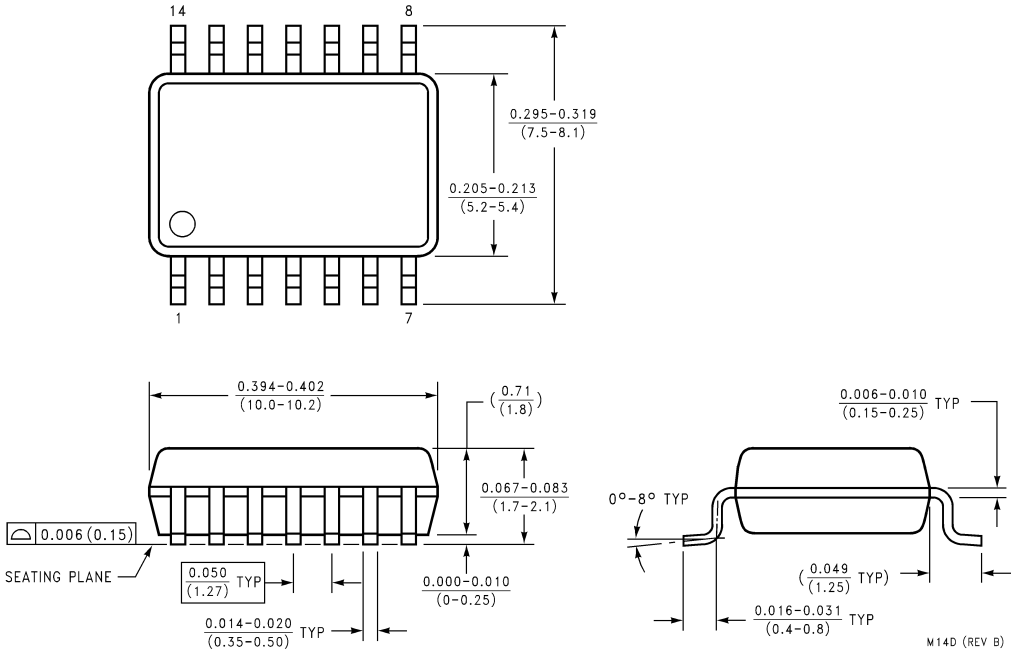
Note 10: C_{PD} is measured at 10 MHz.

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Molded Small Outline Integrated Circuit, JEDEC (SC)
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded Small Outline Package, EIAJ (SJ)
Package Number M14D

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FAIRCHILD SEMICONDUCTOR TM

May 1998

74LVQ86
Low Voltage Quad 2-Input Exclusive-OR Gate

General Description

The LVQ86 contains four 2-input exclusive-OR gates.

Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

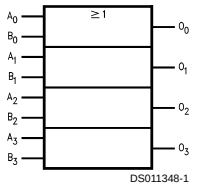
Ordering Code:

Order Number	Package Number	Package Description
74LVQ86SC	M14A	14-Lead (0.150" Wide) Molded Small Outline Package, SOIC JEDEC
74LVQ86SJ	M14D	14-Lead Small Outline Package, SOIC EIAJ

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

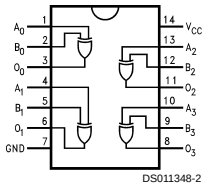
IEEE/IEC



DS011348-1

Connection Diagram

Pin Assignment
SOIC JEDEC and EIAJ



DS011348-2

Pin Descriptions

Pin Names	Description
A_0–A_3	Inputs
B_0–B_3	Inputs
O_0–O_3	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±200 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±100 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	
LVQ	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74LVQ	−40˚C to +85˚C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation .

Note 2: Unused inputs must be held HIGH or LOW.. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C		T_A = −40˚C to +85˚C	Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44		V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}	Output Current	3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	μA	V_{IN} = V_{CC} or GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.8	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.8	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 20 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n − 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

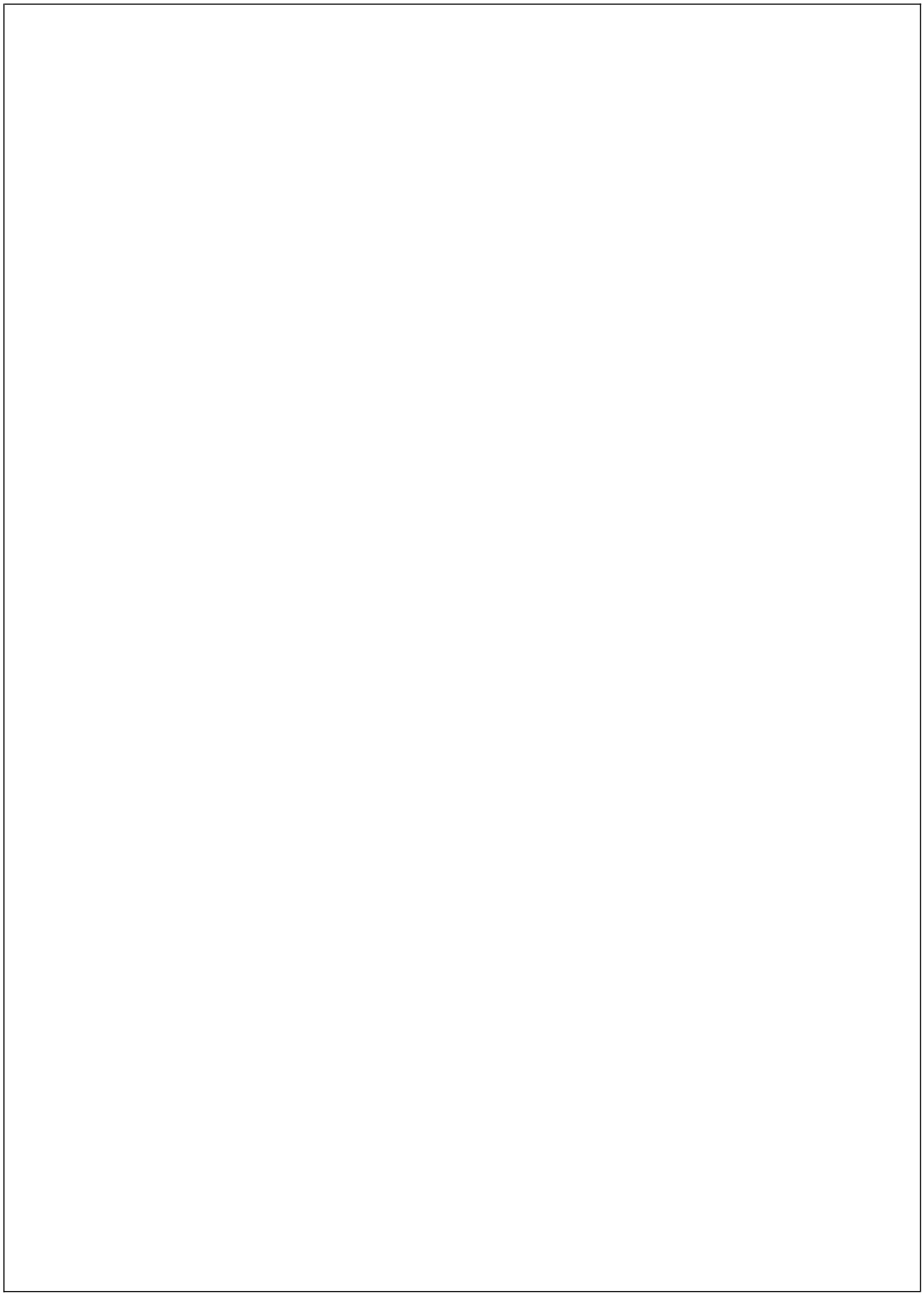
Symbol	Parameter	V_{CC} (V)	T_A = +25°C, C_L = 50 pF			T_A = −40°C to +85°C, C_L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	2.7	2.0	7.2	16.2	1.5	18.0	ns
		3.3 ±0.3	2.0	6.0	11.5	1.5	12.5	
t_{PHL}	Propagation Delay	2.7	2.0	7.8	16.2	1.5	18.0	ns
		3.3 ±0.3	2.0	6.5	11.5	1.5	12.5	
t_{OSHL},	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	(Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skews defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

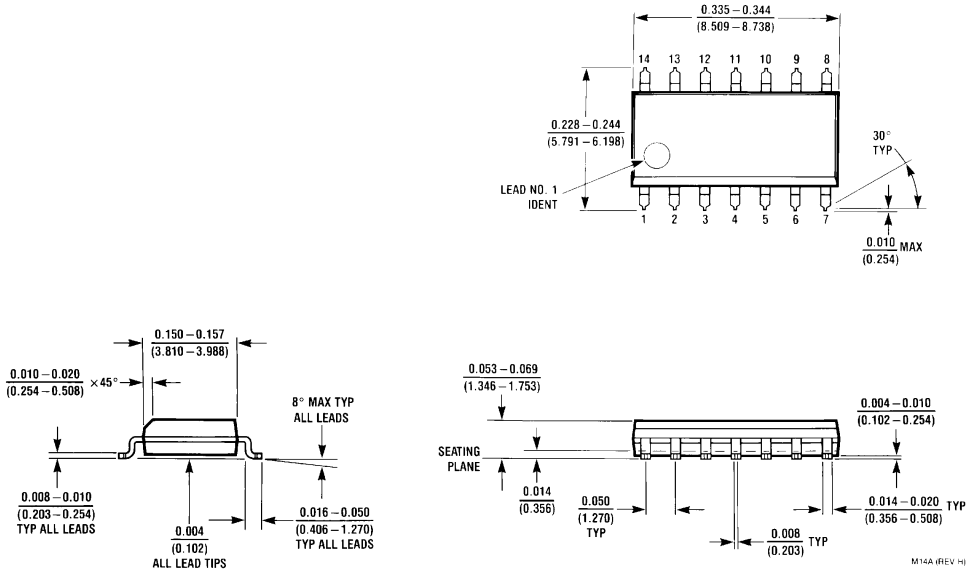
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	23	pF	V_{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

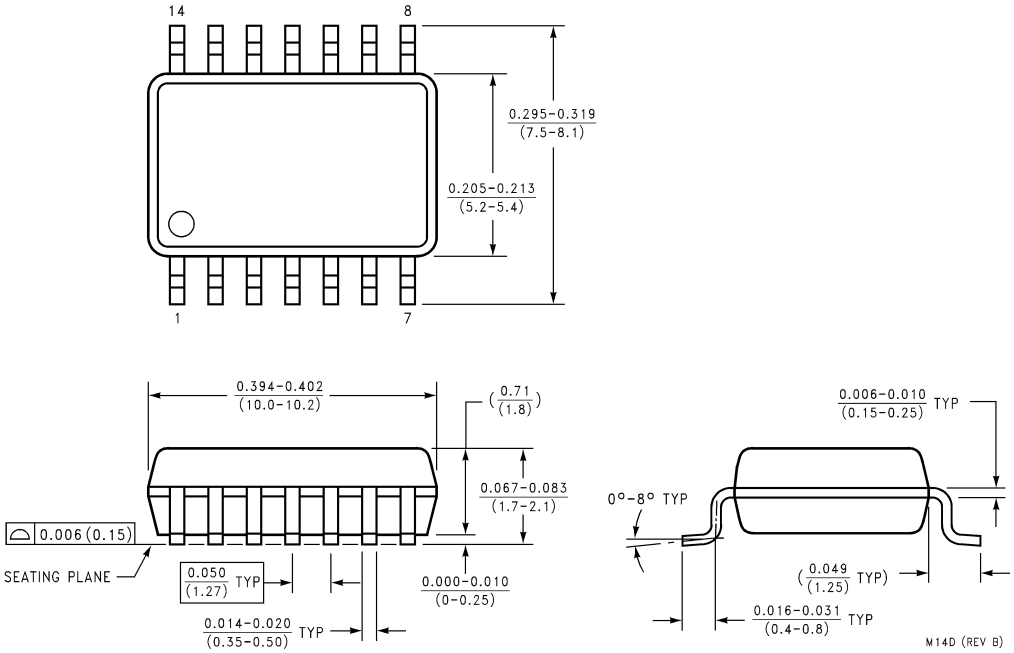


Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead (0.150" Wide) Molded Small Outline Package, SOIC JEDEC
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Small Outline Package, SOIC EIAJ
Package Number M14D

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

PRELIMINARY
November 1996

74LVT125
3.3V ABT Quad Buffer with TRI-STATE® Outputs

General Description

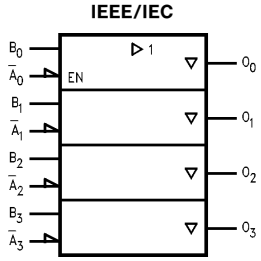
The LVT125 contains four independent non-inverting buffers with TRI-STATE outputs.

These buffers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT125 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

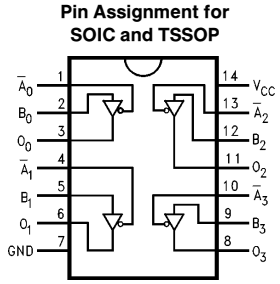
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SOIC JEDEC, SOIC EIAJ, and TSSOP
- Functionally compatible with the 74 series 125
- Latch-up performance exceeds 500 mA

Logic Symbol



TL/F/12011–1

Connection Diagram



TL/F/12011–2

Pin Names	Description
$\overline{A}_n$, B_n	Inputs
O_n	TRI-STATE Outputs

Truth Table

Inputs		Output
A_n	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

	SOIC JEDEC	SOIC EIAJ	TSSOP
Order Number	74LVT125M 74LVT125MX	74LVT125SJ 74LVT125SJX	74LVT125MTC 74LVT125MTCX
See NS Package Number	M14A	M14D	MTC14

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in TRI-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	−50	$V_O < GND$	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at High State	mA
		128	$V_O > V_{CC}$ Output at Low State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the ''Electrical Characteristics'' table are not guaranteed at the Absolute Maximum Ratings. The ''Recommended Operating Conditions'' table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	3.6	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
		TRI-STATE	0	5.5	
I_{OH}	High-Level Output Current			−32	mA
I_{OL}	Low-Level Output Current			64	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage	2.7–3.6			0.8		
V_{OH}	Output HIGH Voltage	2.7–3.6	$V_{CC} - 0.2$			V	$I_{OH} = -100\ \mu A$
		2.7	2.4			V	$I_{OH} = -8$ mA
		3.0	2.0			V	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage	2.7			0.2	V	$I_{OL} = 100\ \mu A$
		2.7			0.5	V	$I_{OL} = 24$ mA
		3.0			0.4	V	$I_{OL} = 16$ mA
		3.0			0.5	V	$I_{OL} = 32$ mA
		3.0			0.55	V	$I_{OL} = 64$ mA

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
				Min	Typ (Note 3)	Max		
$I_{I(HOLD)}$	Bus-Hold Input Minimum Drive		3.0	75			μA	$V_I = 0.8V$
				−75			μA	$V_I = 2.0V$
$I_{I(OD)}$	Bus-Hold Input Over-Drive Current to Change State		3.0	500			μA	(Note 4)
				−500			μA	(Note 5)
I_I	Input Current		3.6			10	μA	$V_I = 5.5V$
		Control Pins	3.6			±1	μA	$V_I = 0V$ or V_{CC}
		Data Pins	3.6			−5	μA	$V_I = 0V$
						1	μA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0			±100	μA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$ (Note 6)	Power up/down TRI-STATE Output Current		0–1.2V			±100	μA	$V_O = 0.5V$ to V_{CC} V_I = GND or V_{CC}
I_{OZL}	TRI-STATE Output Leakage Current		3.6			−5	μA	$V_O = 0.5V$
I_{OZH}	TRI-STATE Output Leakage Current		3.6			5	μA	$V_O = 3.0V$
I_{OZH}^+	TRI-STATE Output Leakage Current		3.6			10	μA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current		3.6			7	mA	Outputs Low
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled
I_{CCZ}^+	Power Supply Current		3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)		3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 6: This parameter is valid for any V_{CC} between 0V and 1.2V at 25°C only.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 3)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.0		4.0	1.0	4.5	ns
t_{PHL}		1.0		3.9	1.0	4.9	
t_{PZH}	Output Enable Time	1.0		4.7	1.0	6.0	ns
t_{PZL}		1.0		4.7	1.0	6.5	
t_{PHZ}	Output Disable Time	1.8		5.1	1.8	5.7	ns
t_{PLZ}		1.8		4.5	1.8	4.0	
t_{OSHL}	Output to Output Skew (Note 10)			1.0			ns
t_{OSLH}							

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

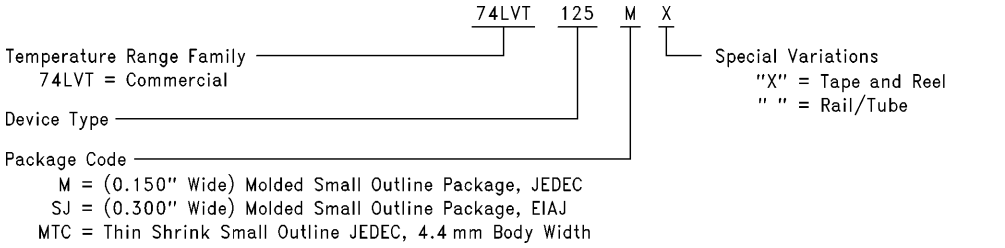
Capacitance (Note 11)

Symbol	Parameter	Min	Typ	Max	Units	Conditions
C_{IN}	Input Capacitance		4		pF	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}
C_{OUT}	Output Capacitance		8		pF	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}

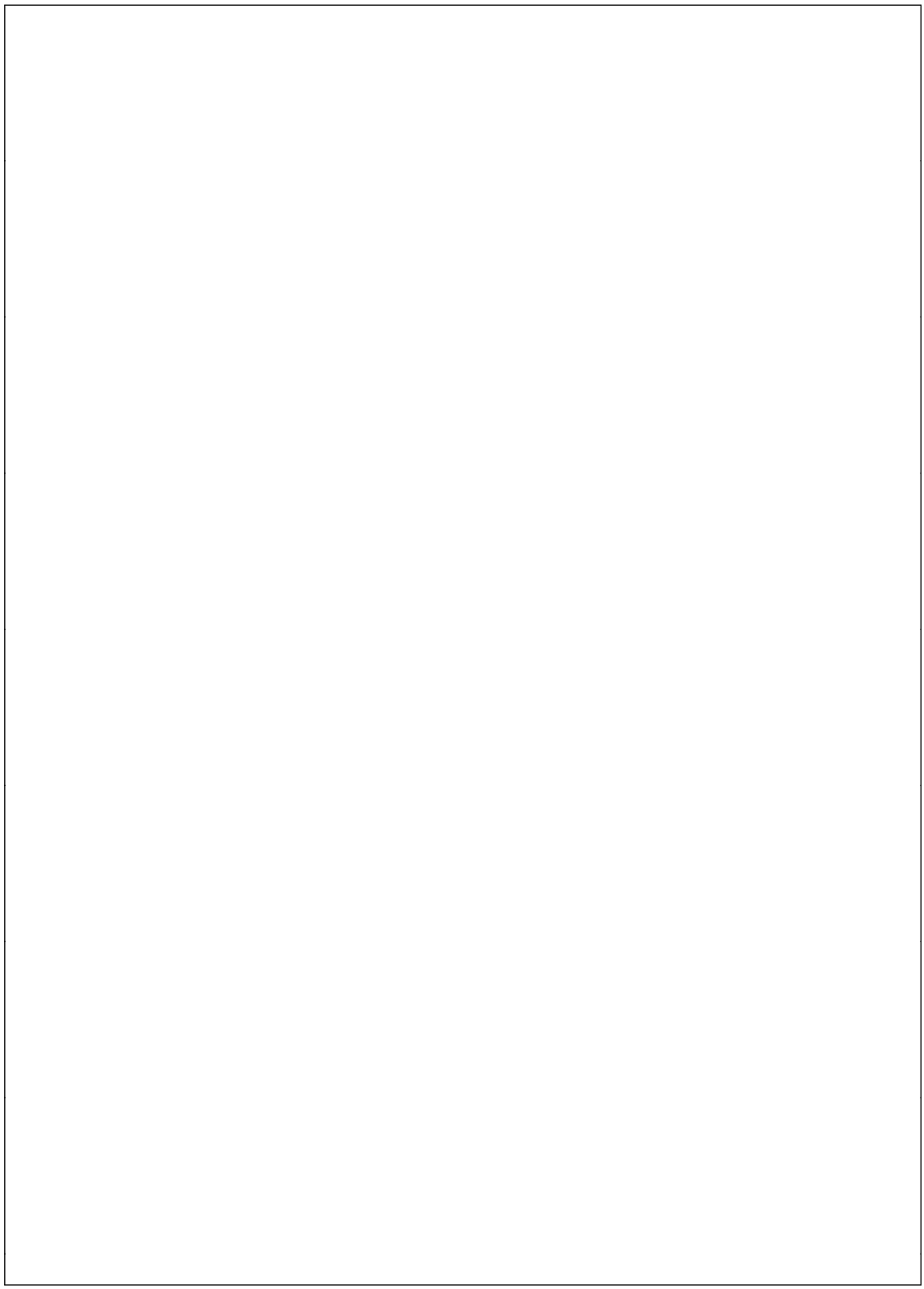
Note 11: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

74LVT125 Ordering Information

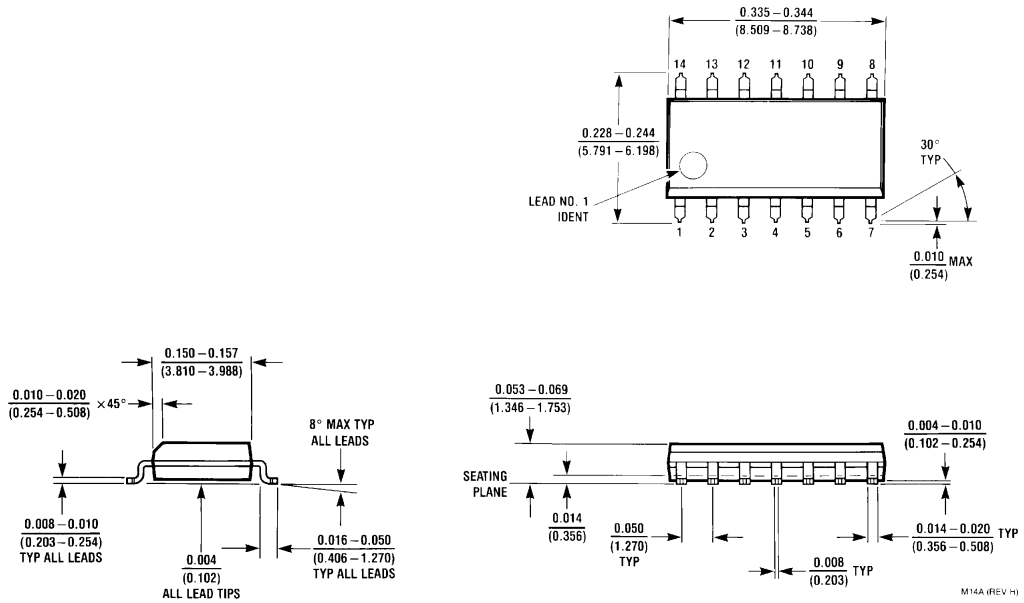
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



TL/F/12011–3

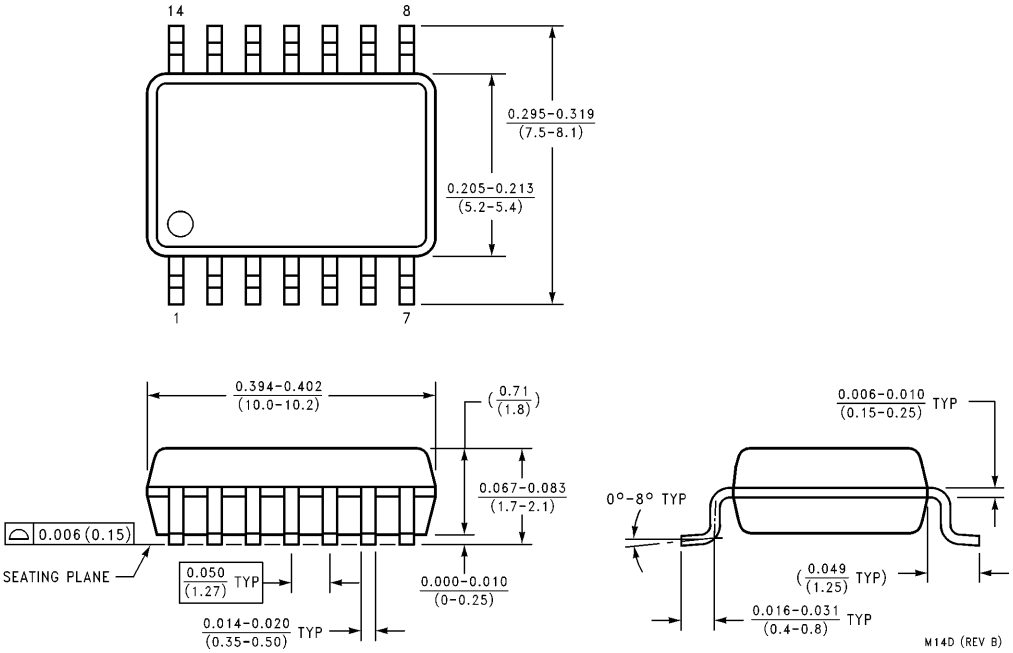


Physical Dimensions inches (millimeters) unless otherwise noted



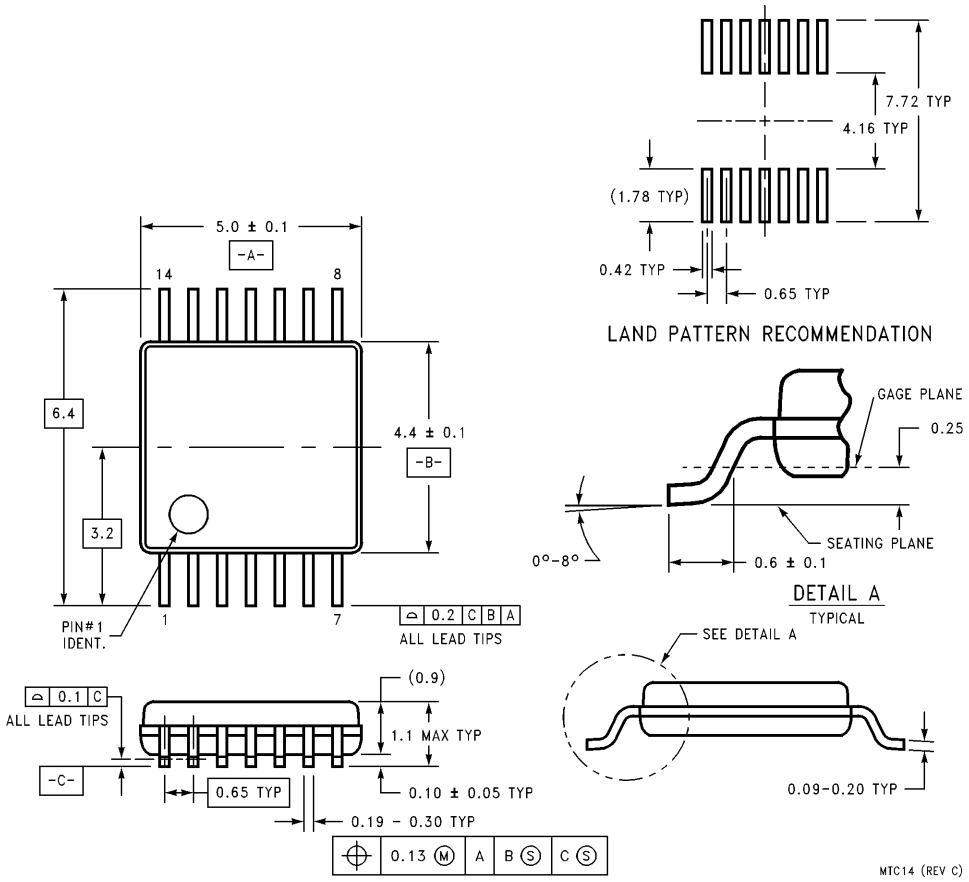
14-Lead (0.150″ Wide) Molded Small Outline Package, JEDEC
Order Number 74LVT125M or 74LVT125MX
See NS Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead (0.300″ Wide) Molded Small Outline Package, EIAJ
Order Number 74LVT125SJ or 74LVT125SJX
See NS Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded Thin Shrink Small Outline Package, JEDEC
Order Number 74LVT125MTC or 74LVT125MTCX
See NS Package Number MTC14

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1999
Revised June 1999

74LVT162240 • 74LVTH162240
Low Voltage 16-Bit Inverting Buffer/Line Driver with 3-STATE Outputs and 25Ω Series Resistors in the Outputs

General Description

The LVT162240 and LVTH162240 contain sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The LVT162240 and LVTH162240 are designed with equivalent 25Ω series resistance in both the HIGH and LOW states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The LVTH162240 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These inverting buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT162240 and LVTH162240 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

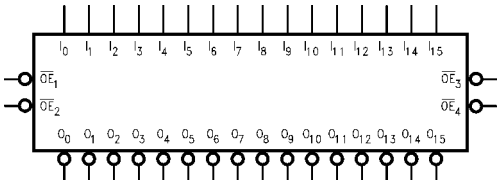
- Input and output interface capability to systems at 5V V_{CC}
- Outputs include equivalent series resistance of 25Ω to make external termination resistors unnecessary and reduce overshoot and undershoot
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH162240), also available without bushold feature (74LVT162240).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Functionally compatible with the 74 series 162240
- Latch-up performance exceeds 500 mA

Ordering Code:

Order Number	Package Number	Package Description
74LVT162240MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT162240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH162240MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH162240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

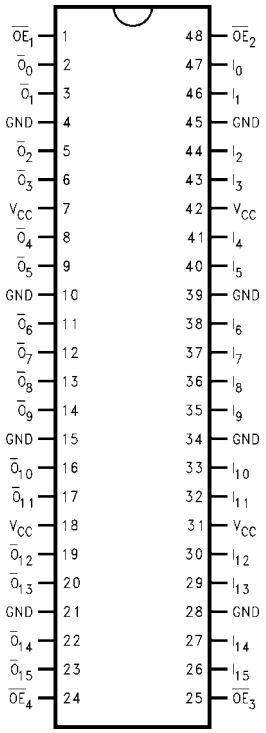
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	3-STATE Outputs

Connection Diagram



Truth Table

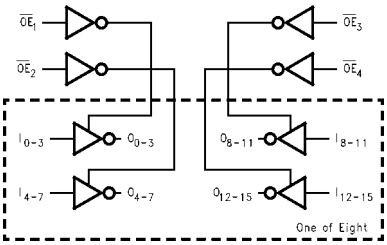
Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z
Inputs		**Outputs**
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z
Inputs		**Outputs**
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z
Inputs		**Outputs**
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level L = LOW Voltage Level
X = Immaterial Z = High Impedance

Functional Description

The LVT162240 and LVTH162240 contain sixteen inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−12	mA
I_{OL}	LOW-Level Output Current		12	mA
T_A	Free Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC}–0.2			V	I_{OH} = −100 µA
			3.0	2.0				I_{OH} = −12 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			3.0			0.8		I_{OL} = 12 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0			±100	µA	0V ≤ V_I or V_O ≤ 5.5V
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V, V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V
I_{OZH^+}	3-STATE Output Leakage Current		3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH162240).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.0		4.0	1.0	4.8	ns
t_{PHL}		1.0		4.0	1.0	4.6	
t_{PZH}	Output Enable Time	1.0		4.8	1.0	5.7	ns
t_{PZL}		1.0		4.9	1.0	6.1	
t_{PHZ}	Output Disable Time	2.0		4.9	2.0	5.4	ns
t_{PLZ}		2.0		4.5	2.0	4.5	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

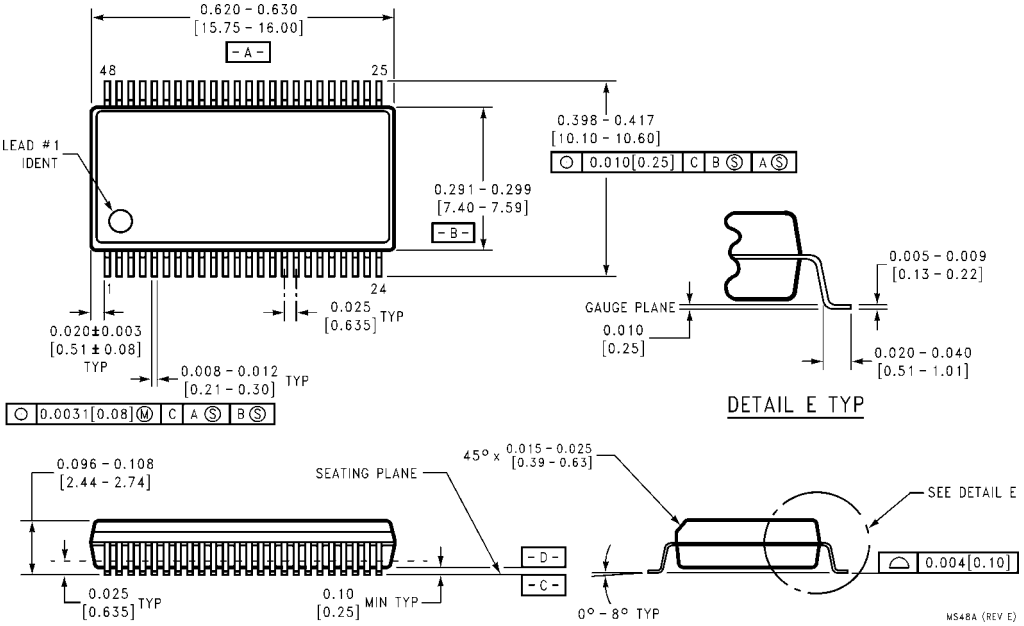
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

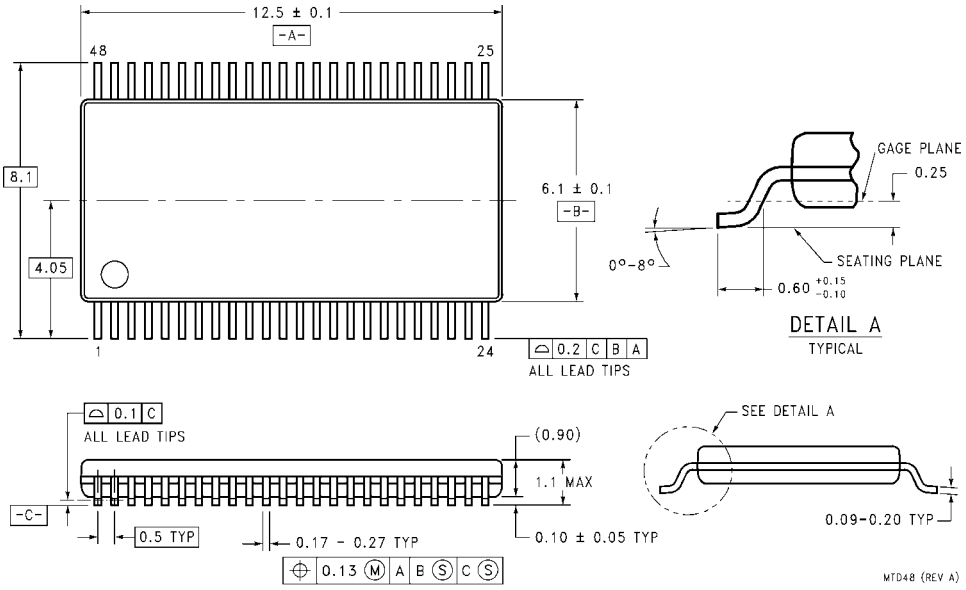
Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1999
Revised June 1999

74LVT162244 • 74LVTH162244
Low Voltage 16-Bit Buffer/Line Driver with 3-STATE Outputs and 25Ω Series Resistors in the Outputs

General Description

The LVT162244 and LVTH162244 contain sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The LVT162244 and LVTH162244 are designed with equivalent 25Ω series resistance in both the HIGH and LOW states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The LVTH162244 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT162244 and LVTH162244 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

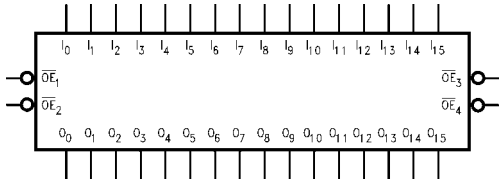
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH162244), also available without bushold feature (74LVT162244).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs include equivalent series resistance of 25Ω to make external termination resistors unnecessary and reduce overshoot and undershoot
- Functionally compatible with the 74 series 162244
- Latch-up performance exceeds 500 mA

Ordering Code:

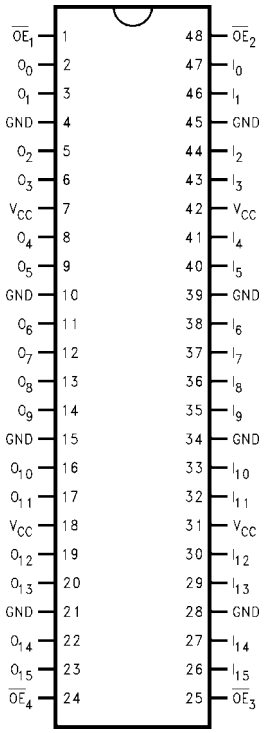
Order Number	Package Number	Package Description
74LVT162244MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT162244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH162244MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH162244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

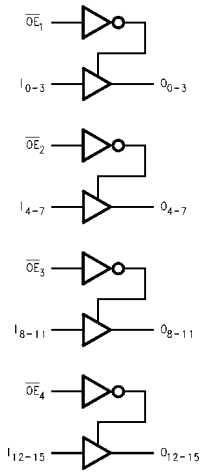
Truth Table

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

Functional Description

The LVT162244 and LVTH162244 contain sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagram



Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−12	mA
I_{OL}	LOW-Level Output Current		12	mA
T_A	Free Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC}−0.2			V	I_{OH} = −100 µA
			3.0	2.0				I_{OH} = −12 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			3.0			0.8		I_{OL} = 12 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V
I_{OZH+}	3-STATE Output Leakage Current		3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH162244).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.4		4.0	1.4	4.8	ns
t_{PHL}		1.2		3.7	1.2	4.1	
t_{PZH}	Output Enable Time	1.2		5.1	1.2	6.5	ns
t_{PZL}		1.4		5.4	1.4	6.9	
t_{PHZ}	Output Disable Time	2.0		5.0	2.0	5.4	ns
t_{PLZ}		1.5		5.0	1.5	5.4	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

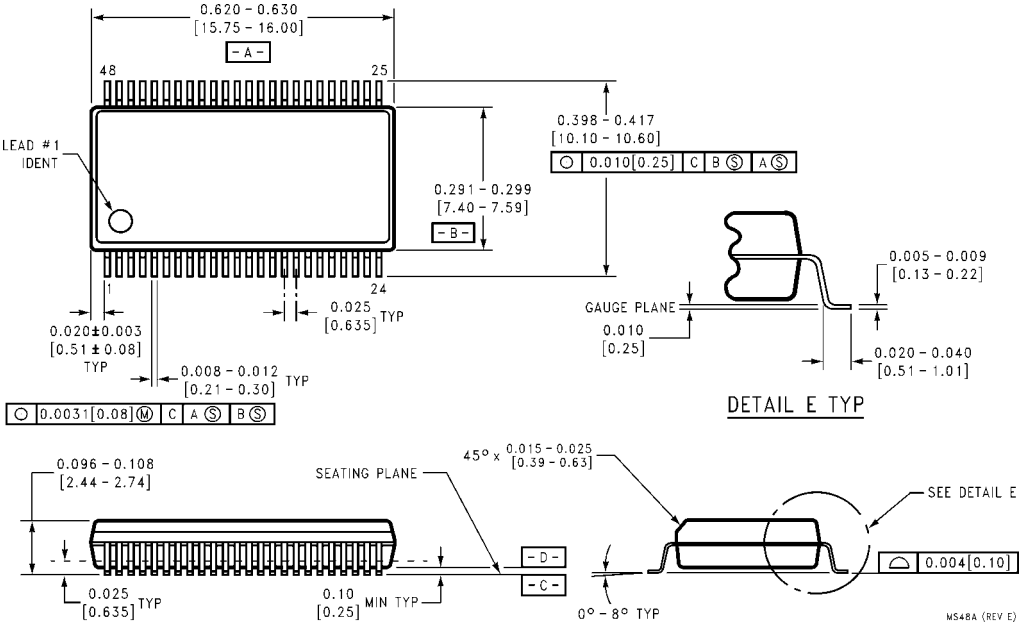
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

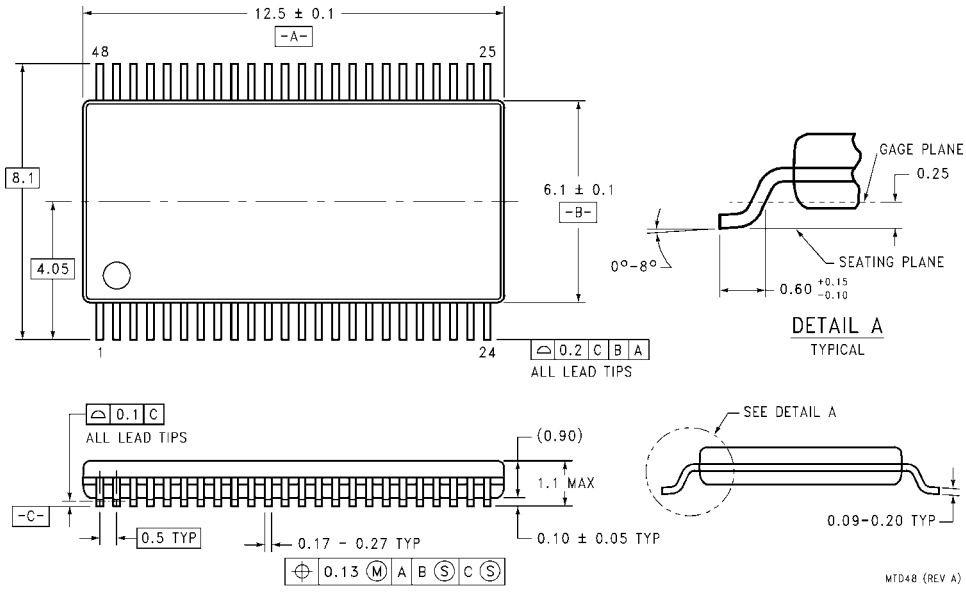
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1999
Revised November 1999

74LVT162245 • 74LVTH162245
Low Voltage 16-Bit Transceiver with 3-STATE Outputs and 25Ω Series Resistors in A Port Outputs

General Description

The LVT162245 and LVTH162245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The LVT162245 and LVTH162245 are designed with equivalent 25Ω series resistance in both the HIGH and LOW states on the A Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The LVTH162245 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These non-inverting transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT162245 and LVTH162245 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH162245), also available without bushold feature (74LVT162245).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- A Port outputs include equivalent series resistance of 25Ω making external termination resistors unnecessary and reducing overshoot and undershoot
- A Port outputs source/sink ±12 mA. B Port outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 162245
- Latch-up performance exceeds 500 mA

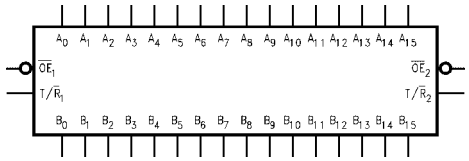
Ordering Code:

Order Number	Package Number	Package Description
74LVT162245MEA (Note 1)	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT162245MTD (Note 1)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH162245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide [TUBE]
74LVTH162245MEX (Note 2)	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide [TAPE and REEL]
74LVTH162245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TUBE]
74LVTH162245MTX (Note 2)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

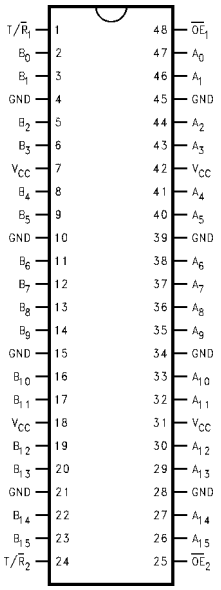
Note 1: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Note 2: Use this Order Number to receive devices in Tape and Reel.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs/3-STATE Outputs
B_0–B_{15}	Side B Inputs/3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH-Z State on A_0–A_7, B_0–B_7

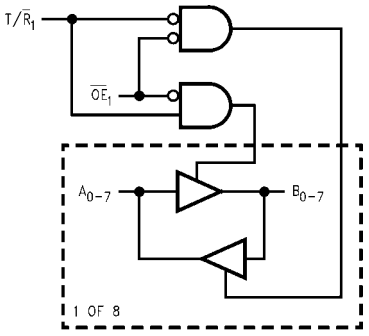
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH-Z State on A_8–A_{15}, B_8–B_{15}

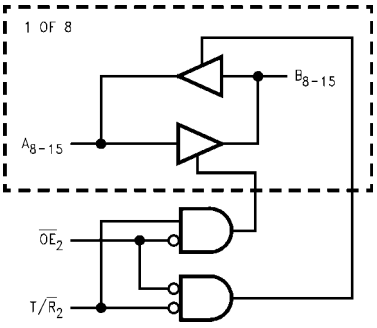
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The LVT162245 and LVTH162245 contain sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagrams





Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 3)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 4)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage		2.7	3.6	V
V_I	Input Voltage		0	5.5	V
I_{OH}	HIGH-Level Output Current	B Port		−32	mA
		A Port		−12	
I_{OL}	LOW-Level Output Current	B Port		64	mA
		A Port		12	
T_A	Free Air Operating Temperature		−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 3: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 4: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$ Min	Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6		0.8	V	
V_{OH}	Output HIGH Voltage	A Port	3.0	2.0		V	$I_{OH} = -12$ mA
			2.7–3.6	$V_{CC}-0.2$		V	$I_{OH} = -100$ µA
		B Port	2.7	2.4		V	$I_{OH} = -8$ mA
			3.0	2.0			$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage	A Port	3.0		0.8	V	$I_{OL} = 12$ mA
			2.7		0.2	V	$I_{OL} = 100$ µA
		B Port	2.7		0.5	V	$I_{OL} = 24$ mA
			3.0		0.4		$I_{OL} = 16$ mA
			3.0		0.5		$I_{OL} = 32$ mA
			3.0		0.55		$I_{OL} = 64$ mA
$I_{I(HOLD)}$ (Note 5)	Bushold Input Minimum Drive		3.0	75		µA	$V_I = 0.8V$
				−75			$V_I = 2.0V$
$I_{I(OD)}$ (Note 5)	Bushold Input Over-Drive Current to Change State		3.0	500		µA	(Note 6)
				−500			(Note 7)
I_I	Input Current		3.6		10	µA	$V_I = 5.5V$
		Control Pins	3.6		±1		$V_I = 0V$ or V_{CC}
		Data Pins	3.6		−5		$V_I = 0V$
					1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0–1.5V		±100	µA	$V_O = 0.5V$ to $3.0V$, V_I = GND to V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	$V_O = 0.5V$
I_{OZL} (Note 5)	3-STATE Output Leakage Current		3.6		−5	µA	$V_O = 0.0V$
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	$V_O = 3.0V$
I_{OZH} (Note 5)	3-STATE Output Leakage Current		3.6		5	µA	$V_O = 3.6V$
$I_{OZH}+$	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 8)		3.6		0.2	mA	One Input at $V_{CC} - 0.6V$, Other Inputs at V_{CC} or GND

Note 5: Applies to Bushold versions only (74LVTH162245).

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 8: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 9)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Min	Typ	Max	Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 10)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 10)

Note 9: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 10: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay Data to A Port Output	1.0	4.0	1.0	4.6	ns
t_{PHL}		1.0	3.7	1.0	4.1	
t_{PLH}	Propagation Delay Data to B Port Output	1.0	3.5	1.0	3.9	ns
t_{PHL}		1.0	3.5	1.0	3.9	
t_{PZH}	Output Enable Time for A Port Output	1.0	5.3	1.0	6.3	ns
t_{PZL}		1.0	5.6	1.0	7.2	
t_{PZH}	Output Enable Time for B Port Output	1.0	4.6	1.0	5.4	ns
t_{PZL}		1.0	5.3	1.0	6.9	
t_{PHZ}	Output Disable Time for A Port Output	1.5	5.6	1.5	6.3	ns
t_{PLZ}		1.5	5.5	1.5	5.5	
t_{PHZ}	Output Disable Time for B Port Output	1.5	5.4	1.5	6.1	ns
t_{PLZ}		1.5	5.1	1.5	5.4	
t_{OSHL}	A Port Output to Output Skew		1.0		1.0	ns
t_{OSLH}	(Note 11)					
t_{OSHL}	B Port Output to Output Skew		1.0		1.0	ns
t_{OSLH}	(Note 11)					

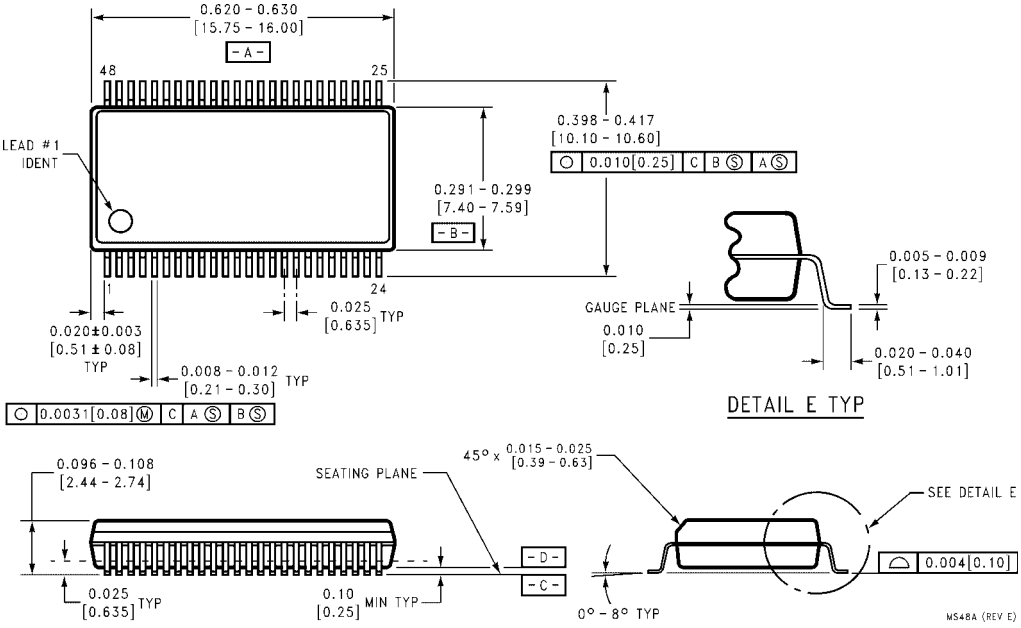
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

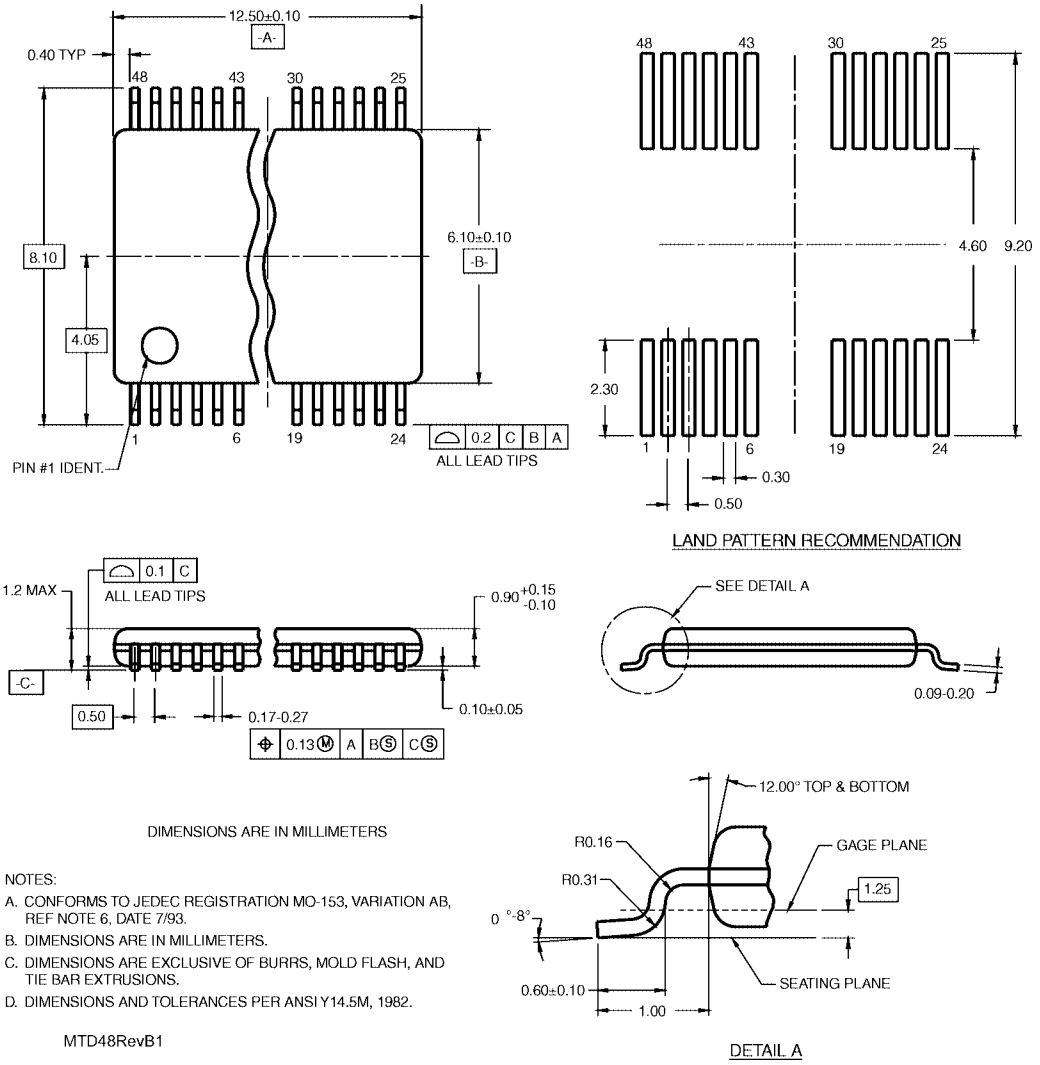
Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1999
Revised March 1999

74LVT16240 • 74LVTH16240
Low Voltage 16-Bit Inverting Buffer/Line Driver with 3-STATE Outputs

General Description

The LVT16240 and LVTH16240 contain sixteen inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is nibble controlled.

Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The LVTH16240 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16240 and LVTH16240 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

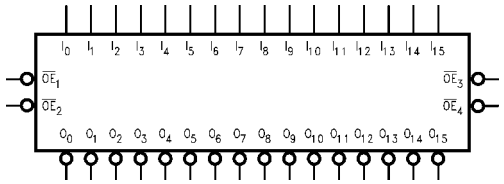
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16240), also available without bushold feature (74LVT16240).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 16240
- Latch-up performance exceeds 500 mA

Ordering Code:

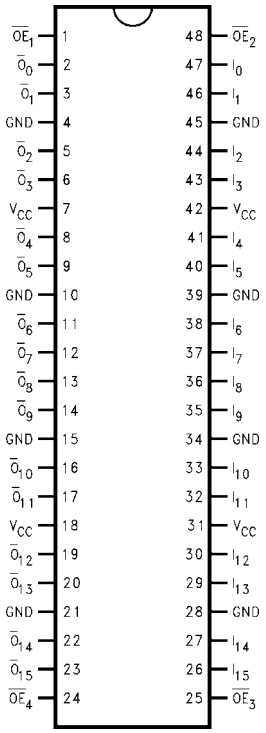
Order Number	Package Number	Package Description
74LVT16240MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16240MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active Low)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	3-STATE Outputs

Truth Table

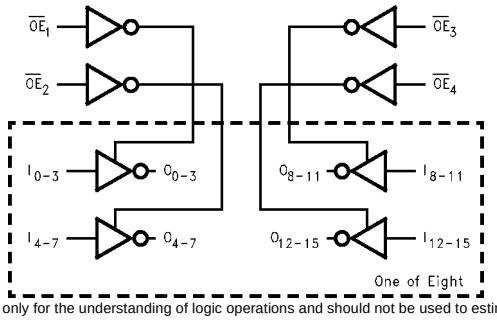
Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z
Inputs		**Outputs**
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z
Inputs		**Outputs**
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z
Inputs		**Outputs**
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The LVT16240 and LVTH16240 contain sixteen inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to V_{CC} + 0.5	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at High State	mA
		128	$V_O > V_{CC}$ Output at Low State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 10)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			2.7	2.4				I_{OH} = −8 mA
			3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5		I_{OL} = 24 mA
			3.0			0.4		I_{OL} = 16 mA
			3.0			0.5		I_{OL} = 32 mA
			3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Output Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 10)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	V_I = GND or V_{CC}, Outputs High
I_{CCL}	Power Supply Current	3.6			5	mA	V_I = GND or V_{CC}, Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	V_I = GND or V_{CC}, Outputs Disabled
I_{CCZH}+	Power Supply Current	3.6			0.19	mA	V_I = GND or V_{CC}, $V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (LVTH16240).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output at LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.0		3.5	1.0	4.2	ns
t_{PHL}		1.0		3.5	1.0	4.0	
t_{PZH}	Output Enable Time	1.0		4.0	1.0	4.9	ns
t_{PZL}		1.2		4.8	1.2	6.1	
t_{PHZ}	Output Disable Time	1.7		4.7	1.7	5.2	ns
t_{PLZ}		1.7		4.2	1.7	4.4	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

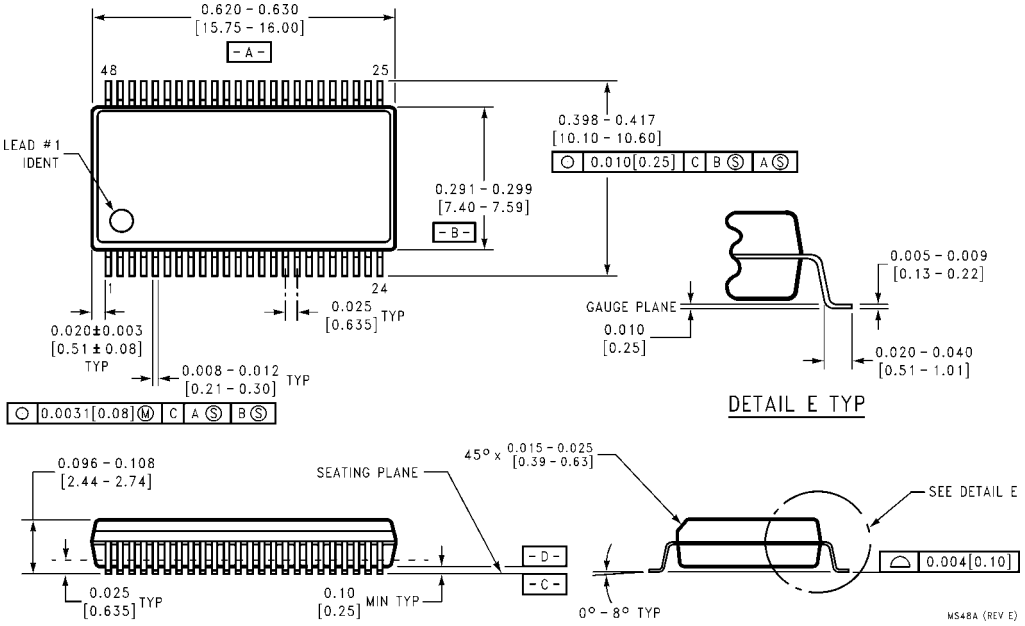
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 12)

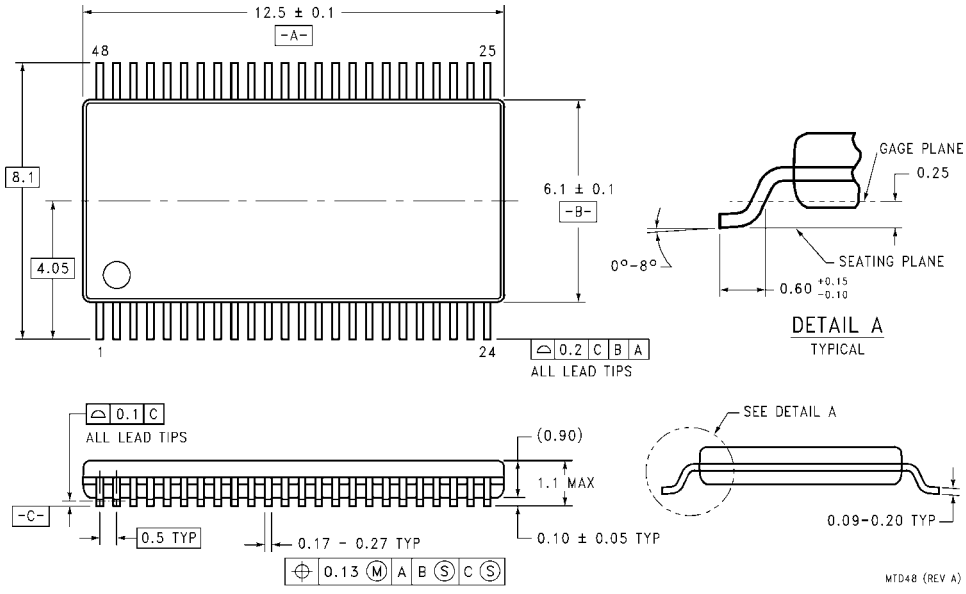
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1999
Revised April 1999

74LVT16244 • 74LVTH16244
Low Voltage16-Bit Buffer/Line Driver with 3-STATE Outputs

General Description

The LVT16244 and LVTH16244 contain sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The LVTH16244 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16244 and LVTH16244 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation

Features

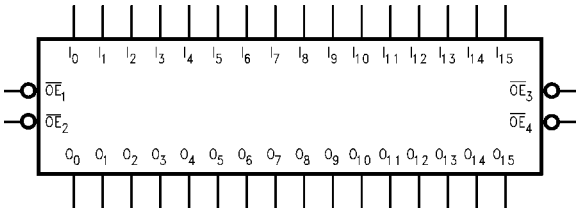
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16244), also available without bushold feature (74LVT16244).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16244
- Latch-up performance exceeds 500 mA

Ordering Code:

Order Number	Package Number	Package Description
74LVT16244MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16244MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



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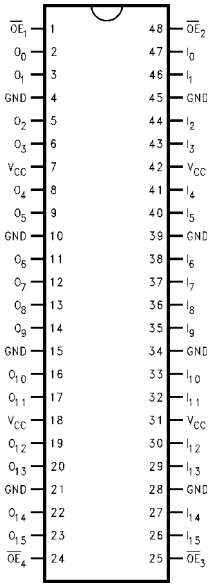
Connection Diagram



Functional Description

The LVT16244 and LVTH16244 contain sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Pin Descriptions

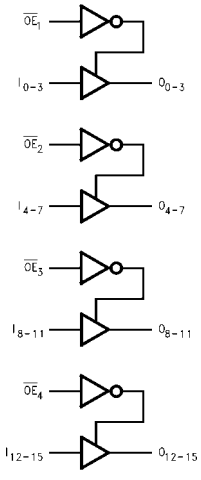
Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active Low)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Truth Table

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z
Inputs		**Outputs**
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z
Inputs		**Outputs**
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z
Inputs		**Outputs**
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			2.7	2.4				I_{OH} = −8 mA
			3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5		I_{OL} = 24 mA
			3.0			0.4		I_{OL} = 16 mA
			3.0			0.5		I_{OL} = 32 mA
			3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	0V ≤ V_I or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0 – 1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current	3.6			5.0	mA	Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies tobushold versions only (LVTH16244).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.2		3.5	1.2	3.9	ns
t_{PHL}		1.2		3.5	1.2	3.9	
t_{PZH}	Output Enable Time	1.2		4.0	1.2	5.0	ns
t_{PZL}		1.2		5.0	1.2	6.5	
t_{PHZ}	Output Disable Time	2.0		4.7	2.0	5.2	ns
t_{PLZ}		1.5		4.2	1.5	4.4	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

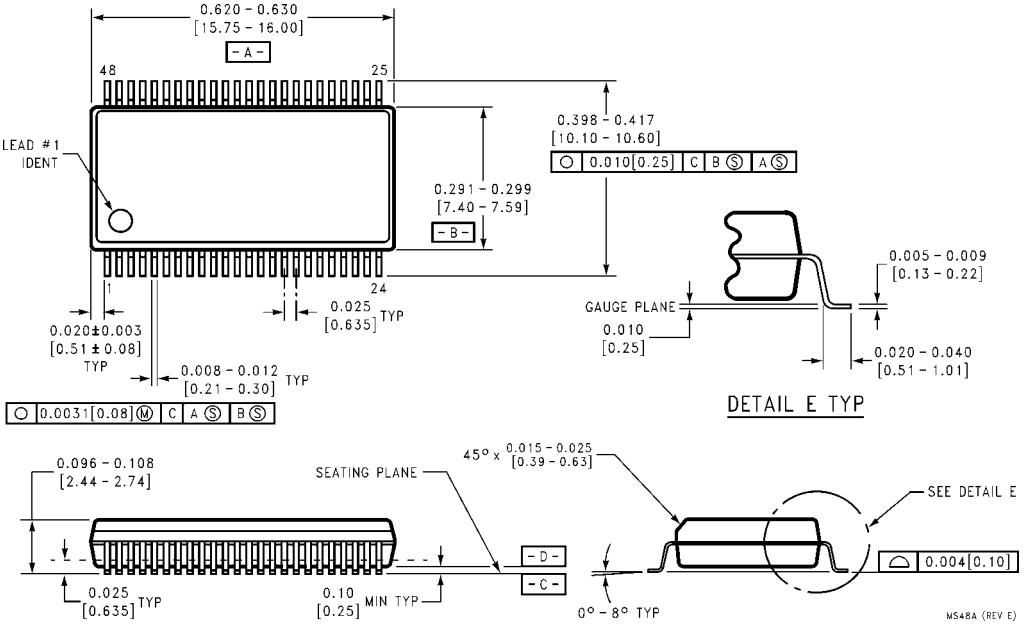
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 12)

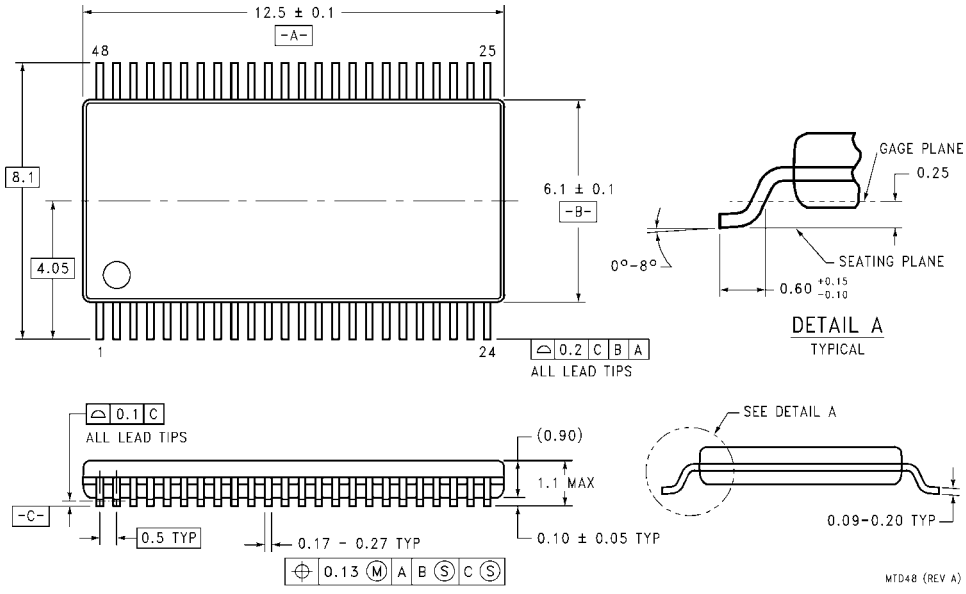
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1999
Revised January 1999

74LVT16244A • 74LVTH16244
Low Voltage16-Bit Buffer/Line Driver with 3-STATE Outputs (Preliminary)

General Description

The LVT16244A and LVTH16244 contain sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The LVTH16244 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16244A and LVTH16244 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation

Features

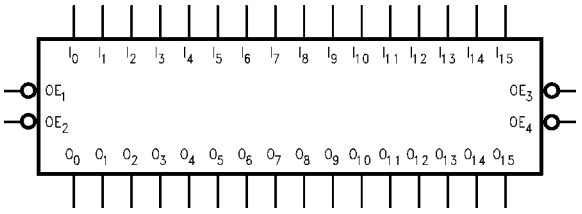
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16244), also available without bushold feature (74LVT16244A).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16244
- Latch-up performance exceeds 500 mA

Ordering Code:

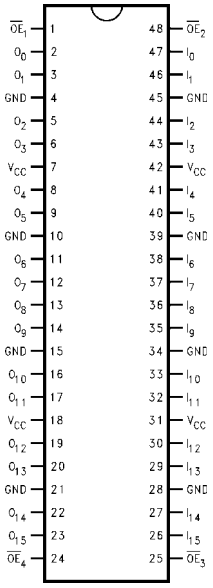
Order Number	Package Number	Package Description
74LVT16244AMEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16244AMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16244MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Functional Description

The LVT16244A and LVTH16244 contain sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Pin Descriptions

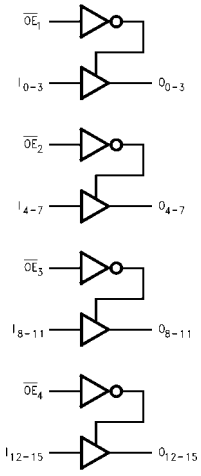
Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active Low)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Truth Table

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z
Inputs		**Outputs**
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z
Inputs		**Outputs**
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z
Inputs		**Outputs**
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			2.7	2.4				I_{OH} = −8 mA
			3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5		I_{OL} = 24 mA
			3.0			0.4		I_{OL} = 16 mA
			3.0			0.5		I_{OL} = 32 mA
			3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bus-Hold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bus-Hold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0 – 1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current	3.6			5.0	mA	Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to Bushold versions only.

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.2		3.5	1.2	3.9	ns
t_{PHL}		1.2		3.5	1.2	3.9	
t_{PZH}	Output Enable Time	1.2		4.0	1.2	5.0	ns
t_{PZL}		1.2		5.0	1.2	6.5	
t_{PHZ}	Output Disable Time	2.2		4.7	2.2	5.2	ns
t_{PLZ}		2.0		4.2	2.0	4.4	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

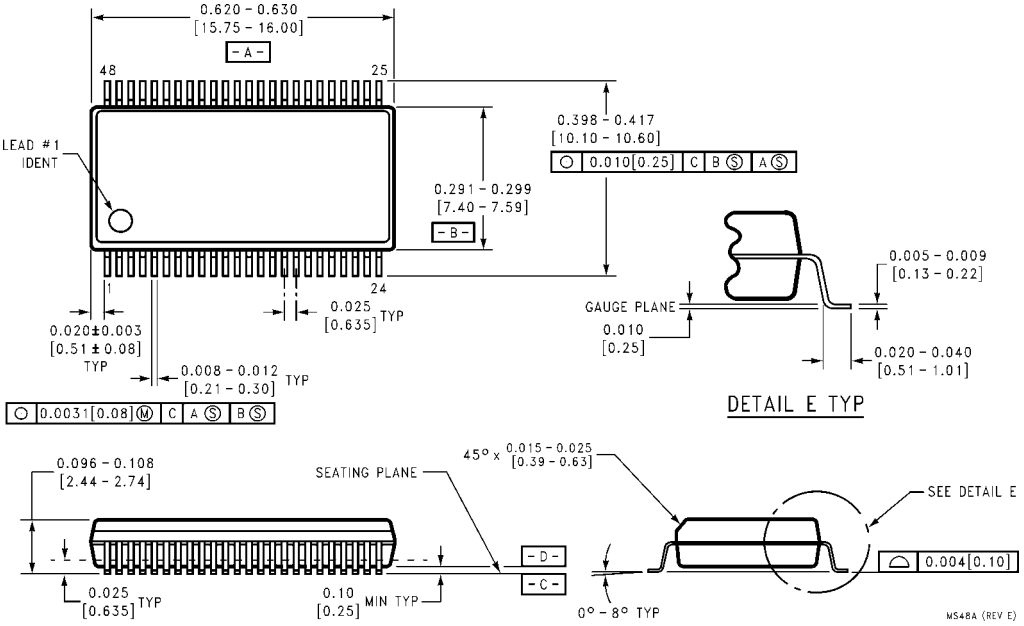
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance (Note 12)

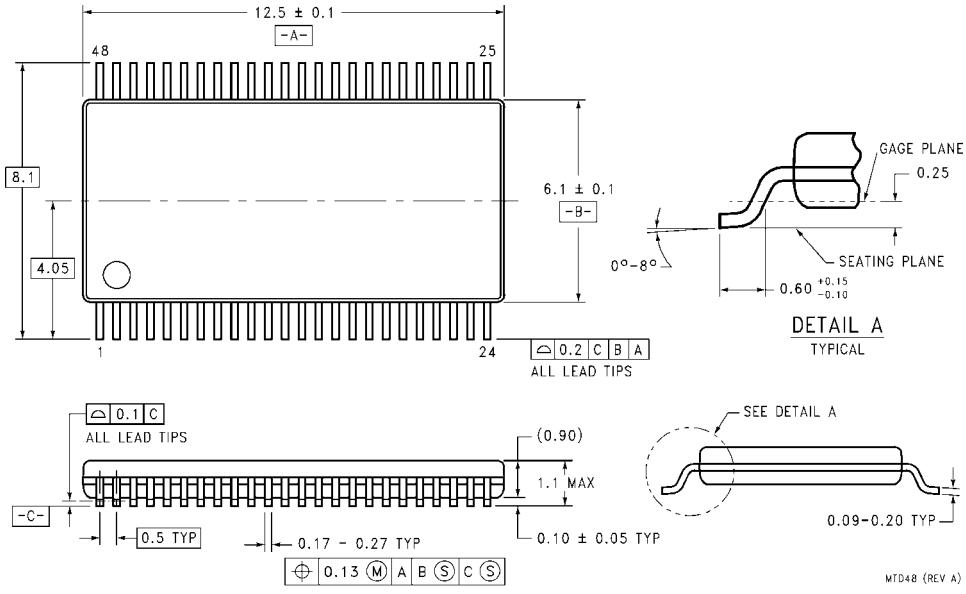
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	9	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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January 1999
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74LVT16245 • 74LVTH16245
Low Voltage 16-Bit Transceiver with 3-STATE Outputs

General Description

The LVT16245 and LVTH16245 contain sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The LVTH16245 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These non-inverting transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16245 and LVTH16245 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

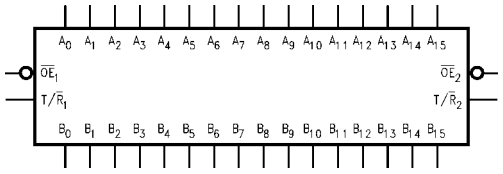
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16245), also available without bushold feature (74LVT16245).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 16245
- Latch-up performance exceeds 500 mA

Ordering Code:

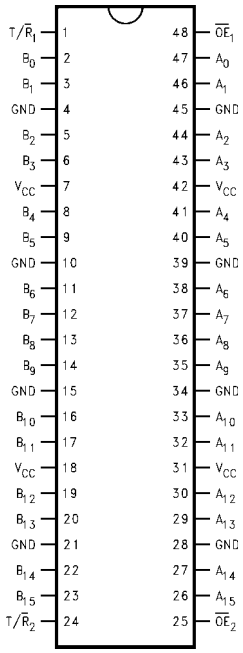
Order Number	Package Number	Package Description
74LVT16245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs/3-STATE Outputs
B_0–B_{15}	Side B Inputs/3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH–Z State on A_0–A_7,B_0–B_7

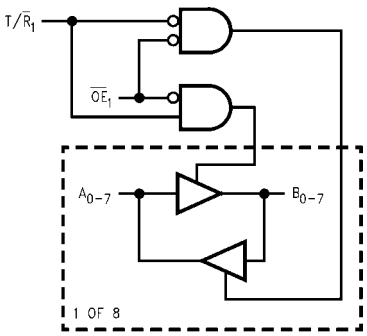
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH–Z State on A_8–A_{15},B_8–B_{15}

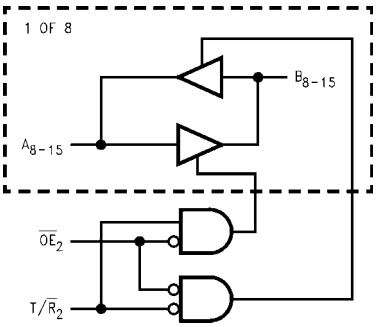
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The LVT16245 and LVTH16245 contain sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagrams





Note: Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	Output at HIGH State, $V_O > V_{CC}$	mA
		128	Output at LOW State, $V_O > V_{CC}$	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature Range	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Ratings must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C		Units	Conditions
				Min	Max		
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \leq$ 0.1V or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8	V	$V_O \geq V_{CC}$ − 0.1V
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 µA
			2.7	2.4			I_{OH} = −8 mA
			3.0	2.0			I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5		I_{OL} = 24 mA
			3.0		0.4		I_{OL} = 16 mA
			3.0		0.5		I_{OL} = 32 mA
			3.0		0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 3)	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
				−75			V_I = 2.0V
$I_{I(OD)}$ (Note 3)	Bushold Input Over-Drive Current to Change State		3.0	500		µA	(Note 4)
				−500			(Note 5)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1		V_I = 0V or V_{CC}
		Data Pins	3.6		−5		V_I = 0V
					1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0		±100	µA	0V ≤ V_I or $V_O \leq$ 5.5V
$I_{PU/PD}$	Power Up/Down 3-STATE Output Current		0–1.5		±100	µA	V_O = 0.5V to 3.0V
							V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.5V
I_{OZL} (Note 3)	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Max		
I_{OZH} (Note 3)	3-STATE Output Leakage Current	3.6		5	μA	$V_O = 3.6V$
$I_{OZH}+$	3-STATE Output Leakage Current	3.6		10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6		5.0	mA	Outputs LOW
I_{CCZ}	Power Supply Current	3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current	3.6		0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 6)	3.6		0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: Applies to bushold versions only (74LVTH16245).

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	(Note 8)

Note 7: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.5	3.5	1.5	3.9	ns
t_{PHL}		1.3	3.5	1.3	3.9	
t_{PZH}	Output Enable Time	1.5	4.5	1.5	5.3	ns
t_{PZL}		1.6	5.3	1.6	6.9	
t_{PHZ}	Output Disable Time	2.3	5.4	2.3	6.1	ns
t_{PLZ}		2.2	5.1	2.2	5.4	
t_{OSHL}	Output to Output Skew		1.0		1.0	ns
t_{OSLH}	(Note 9)					

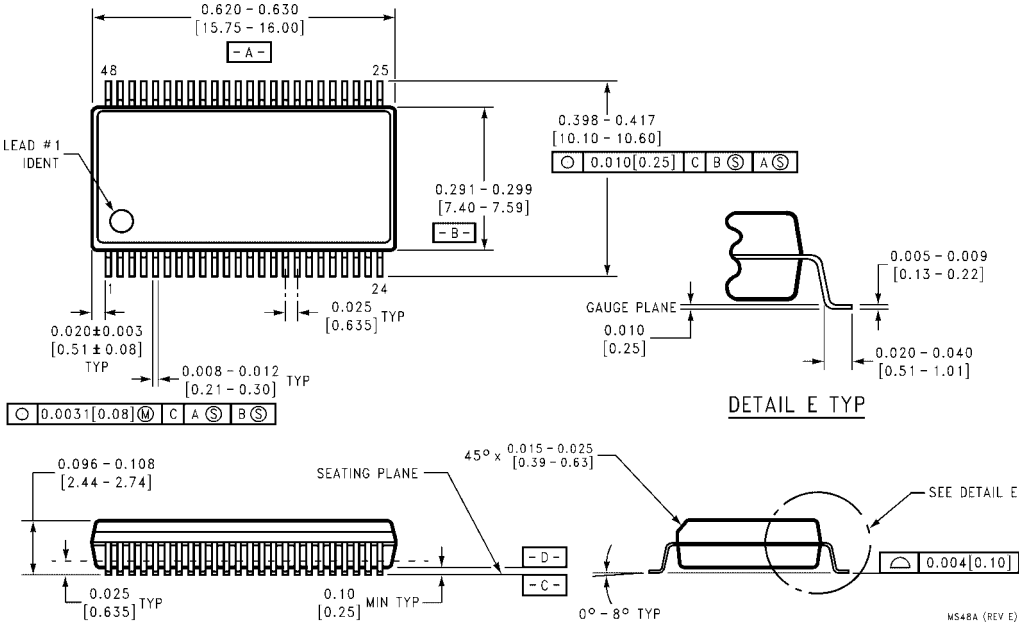
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance (Note 10)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

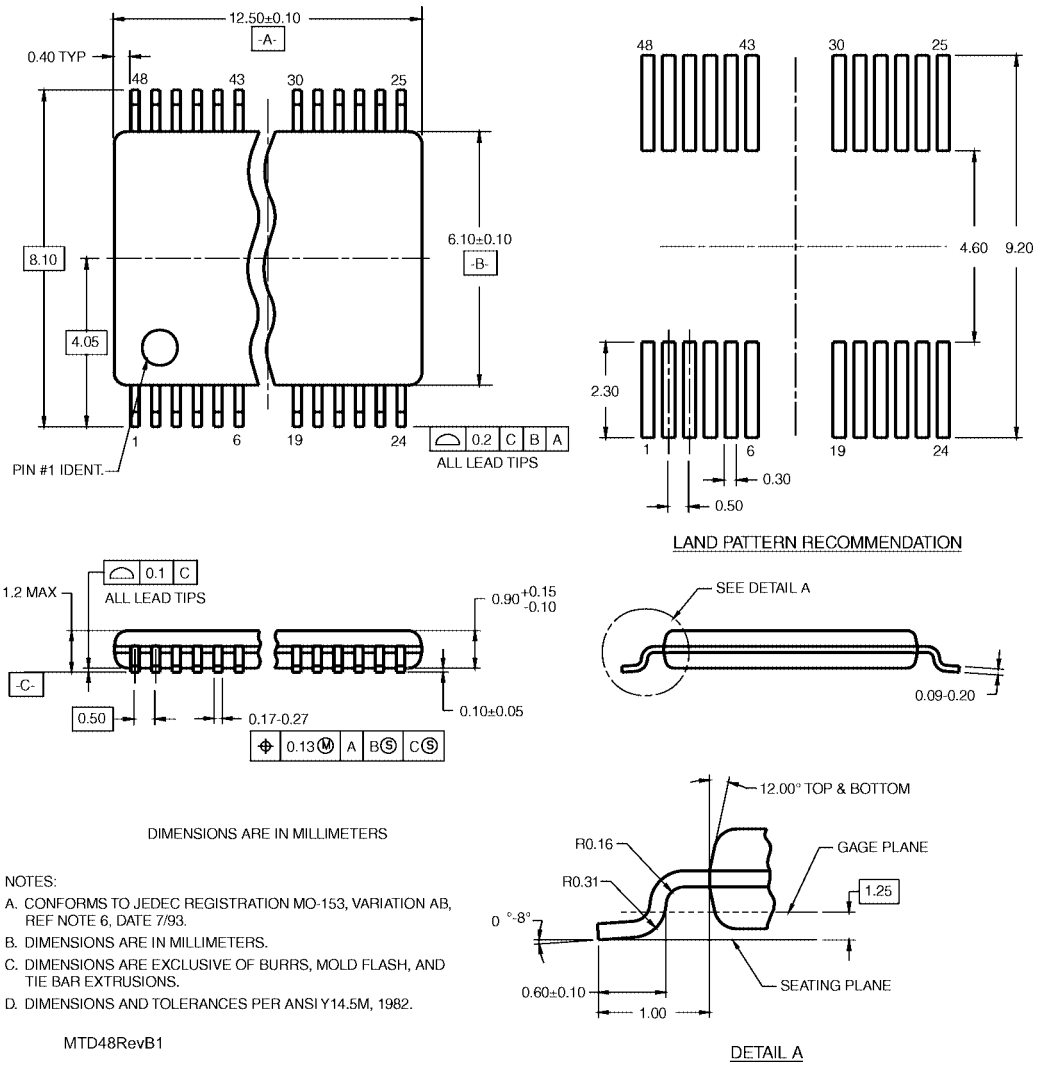
Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1999
Revised February 1999

74LVT16245A • 74LVTH16245
Low Voltage 16-Bit Transceiver with 3-STATE Outputs

General Description

The LVT16245A and LVTH16245 contain sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The LVTH16245 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These non-inverting transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16245A and LVTH16245 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

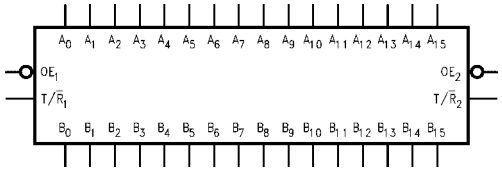
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16245), also available without bushold feature (74LVT16245A).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16245
- Latch-up performance exceeds 500 mA

Ordering Code:

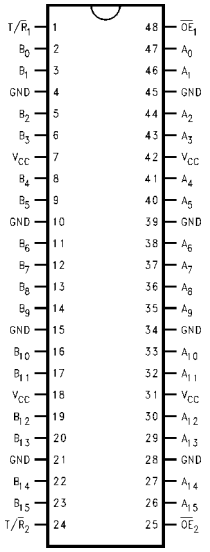
Order Number	Package Number	Package Description
74LVT16245AMEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16245AMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16245MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active Low)
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs/3-STATE Outputs
B_0–B_{15}	Side B Inputs/3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH–Z State on A_0–A_7,B_0–B_7

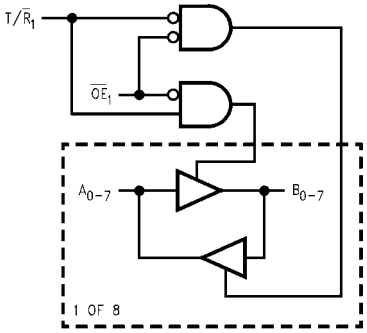
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH–Z State on A_8–A_{15},B_8–B_{15}

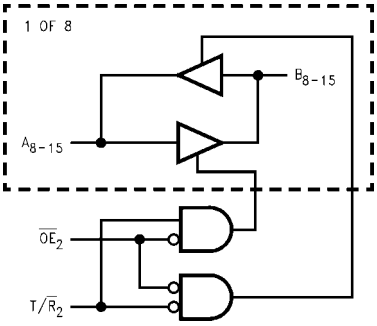
H= High Voltage Level
L= Low Voltage Level
X= Immaterial
Z = High Impedance

Functional Description

The LVT16245A and LVTH16245 contain sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Logic Diagrams





Note: Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	Output at HIGH State, $V_O > V_{CC}$	mA
		128	Output at LOW State, $V_O > V_{CC}$	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature Range	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Ratings must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			2.7	2.4				I_{OH} = −8 mA
			3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5		I_{OL} = 24 mA
			3.0			0.4		I_{OL} = 16 mA
			3.0			0.5		I_{OL} = 32 mA
			3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$	Bus-Hold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
(Note 4)				−75				V_I = 2.0V
$I_{I(OD)}$	Bus-Hold Input Over-Drive		3.0	500			µA	(Note 5)
(Note 4)	Current to Change State			−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Output Current		0–1.5			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			20	µA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current	3.6			5.0	mA	Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to Bushold versions only (74LVTH16245).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.5		3.5	1.5	3.9	ns
t_{PHL}		1.3		3.5	1.3	3.9	
t_{PZH}	Output Enable Time	1.5		4.5	1.5	5.3	ns
t_{PZL}		1.6		5.3	1.6	6.9	
t_{PHZ}	Output Disable Time	2.3		5.4	2.3	6.1	ns
t_{PLZ}		2.2		5.1	2.2	5.4	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

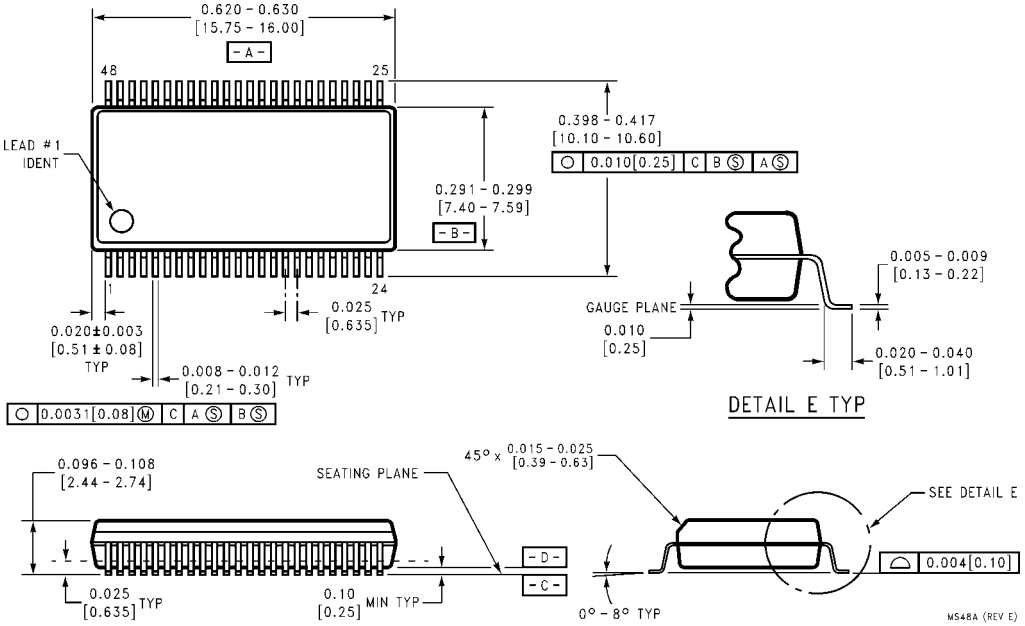
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance (Note 12)

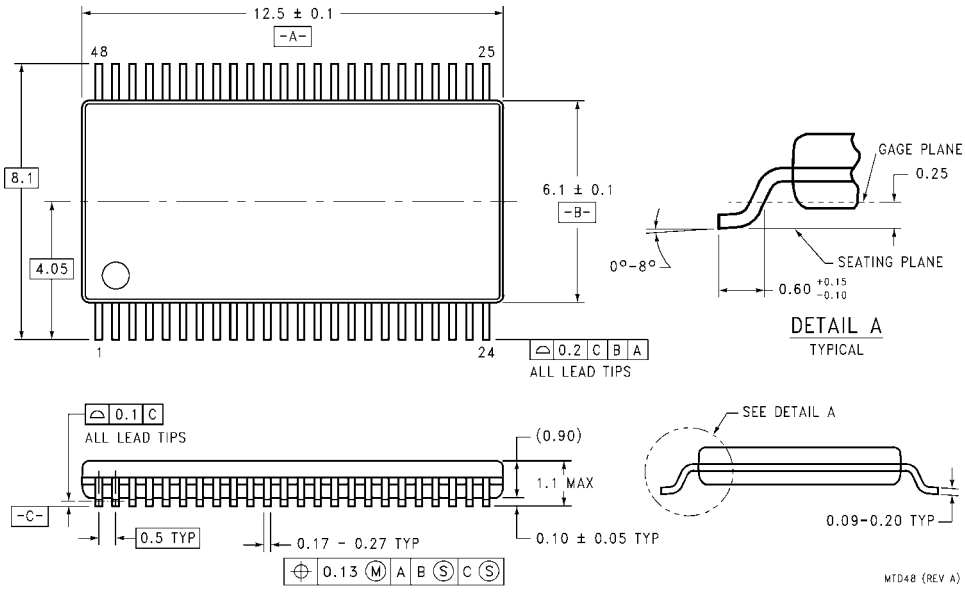
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	10	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1999
Revised April 1999

74LVT16373 • 74LVTH16373
Low Voltage 16-Bit Transparent Latch with 3-STATE Outputs

General Description

The LVT16373 and LVTH16373 contain sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The LVTH16373 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These latches are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16373 and LVTH16373 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

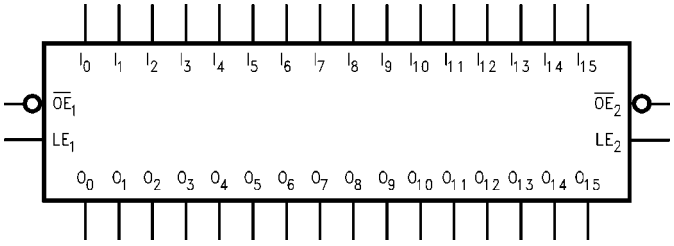
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16373), also available without bushold feature (74LVT16373).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 16373
- Latch-up performance exceeds 500 mA

Ordering Code:

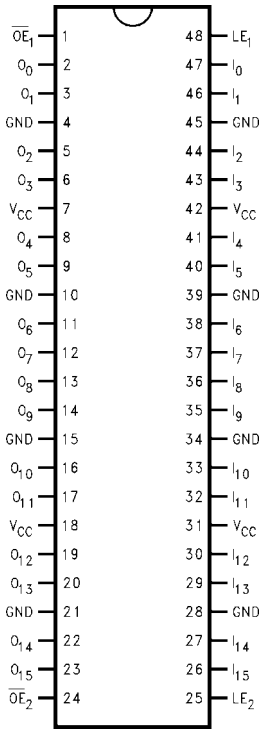
Order Number	Package Number	Package Descripion
74LVT16373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Inputs
O_0–O_{15}	3-STATE Outputs

Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_o

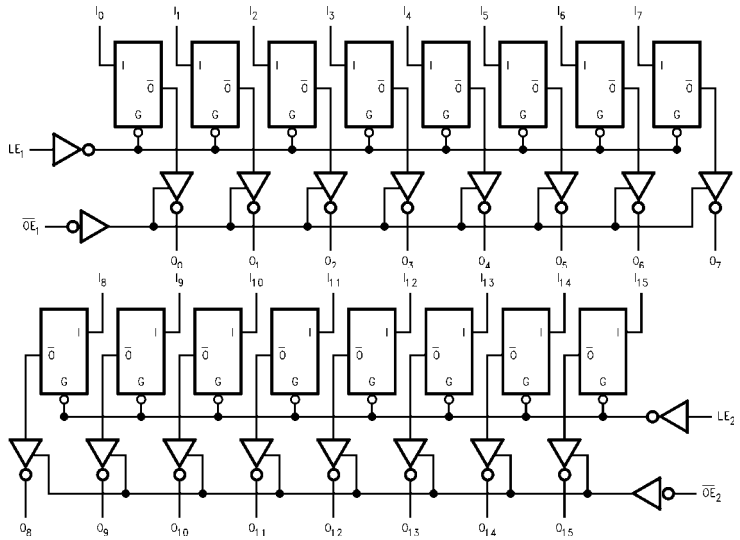
Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_o

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance
O_o = Previous output prior to HIGH to LOW transition of LE

Functional Description

The LVT16373 and LVTH16373 contain sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the D_n enters the latches. In this condition the latches are transparent, i.e, a latch output will change states each time its D input changes. When LE_n is LOW, the latches store information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagrams



Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
			Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage	2.7–3.6			0.8	V	
V_{OH}	Output HIGH Voltage	2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
		2.7	2.4				I_{OH} = −8 mA
		3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage	2.7			0.2	V	I_{OL} = 100 µA
		2.7			0.5		I_{OL} = 24 mA
		3.0			0.4		I_{OL} = 16 mA
		3.0			0.5		I_{OL} = 32 mA
		3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive	3.0	75			µA	V_I = 0.8V
			−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State	3.0	500			µA	(Note 5)
			−500				(Note 6)
I_I	Input Current	3.6			10	µA	V_I = 5.5V
	Control Pins	3.6			±1		V_I = 0V or V_{CC}
	Data Pins	3.6			−5		V_I = 0V
					1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current	0			±100	µA	0V ≤ V_I or V_O ≤ 5.5V
$I_{PU/PD}$	Power up/down 3-STATE Output Current	0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current	3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current	3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH16373).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, C_L=50pF, R_L=500Ω					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5		3.9	1.5	4.3	ns
t_{PLH}	D_n to O_n	1.5		3.8	1.5	4.2	
t_{PHL}	Propagation Delay	1.9		4.2	1.9	4.4	ns
t_{PLH}	LE to O_n	1.6		4.3	1.6	4.8	
t_{PZL}	Output Enable Time	1.3		4.3	1.3	4.9	ns
t_{PZH}		1.0		4.3	1.0	5.1	
t_{PLZ}	Output Disable Time	1.5		4.7	1.5	4.8	ns
t_{PHZ}		2.0		5.0	2.0	5.4	
t_S	Setup Time, D_n to LE	1.0			0.8		ns
t_H	Hold Time, D_n to LE	1.0			1.1		ns
t_W	LE Pulse Width	3.0			3.0		ns
t_{OSHL}	Output to Output Skew (Note 11)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

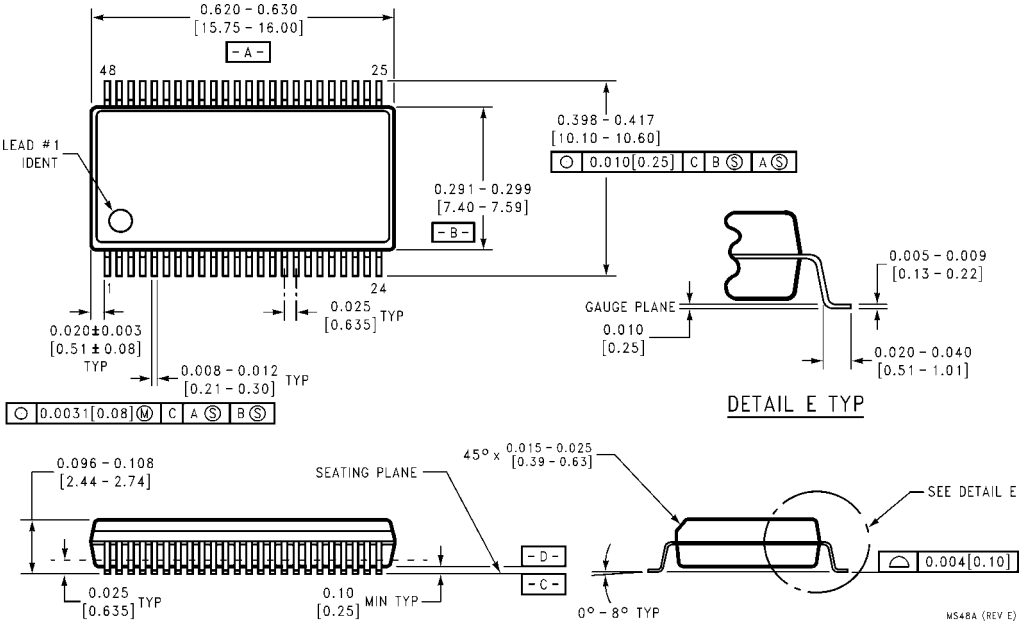
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 12)

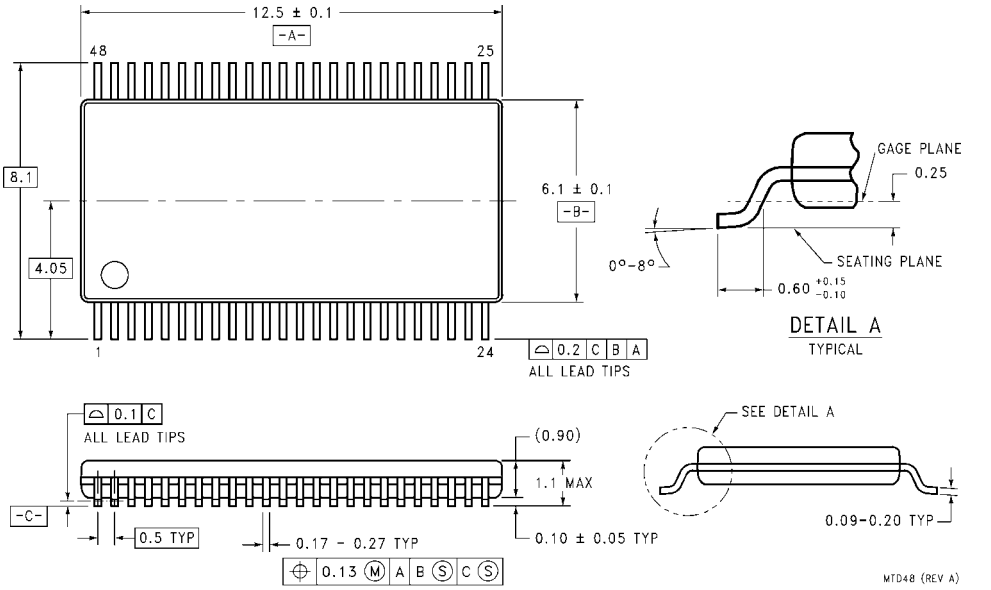
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1999
Revised April 1999

74LVT16374 • 74LVTH16374
Low Voltage 16-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVT16374 and LVTH16374 contain sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and Output Enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

The LVTH16374 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These flip-flops are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16374 and LVTH16374 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

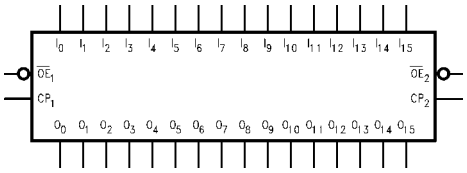
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH16374), also available without bushold feature (74LVT16374).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA

Ordering Code:

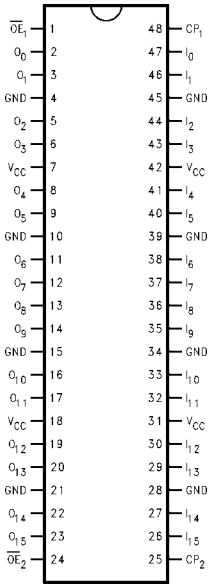
Order Number	Package Number	Package Description
74LVT16374MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVT16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74LVTH16374MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LVTH16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Inputs
O_0–O_{15}	3-STATE Outputs

Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
⌐	L	H	H
⌐	L	L	L
L	L	X	O_o
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
⌐	L	H	H
⌐	L	L	L
L	L	X	O_o
X	H	X	Z

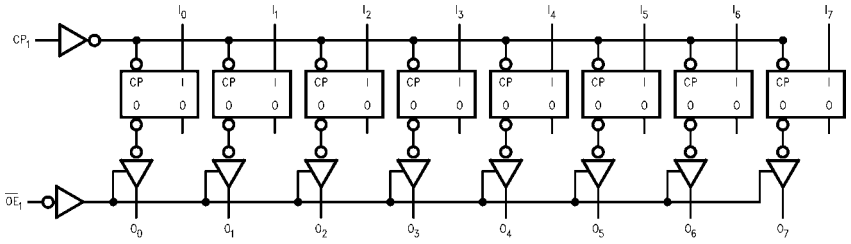
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance
O_o = Previous O_o before HIGH to LOW of CP

Functional Description

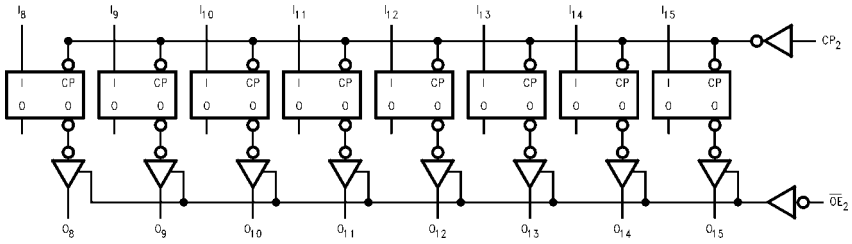
The LVT16374 and LVTH16374 consist of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each byte has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}_n$ input does not affect the state of the flip-flops.

Logic Diagrams

Byte 1 (0:7)



Byte 2 (8:15)



Please note that these diagrams are provided for the understanding of logic operaiton and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at High State	mA
		128	$V_O > V_{CC}$ Output at Low State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
			Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage	2.7–3.6			0.8	V	
V_{OH}	Output HIGH Voltage	2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
		2.7	2.4				I_{OH} = −8 mA
		3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage	2.7			0.2	V	I_{OL} = 100 µA
		2.7			0.5		I_{OL} = 24 mA
		3.0			0.4		I_{OL} = 16 mA
		3.0			0.5		I_{OL} = 32 mA
		3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive	3.0	75			µA	V_I = 0.8V
			−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State	3.0	500			µA	(Note 5)
			−500				(Note 6)
I_I	Input Current	3.6			10	µA	V_I = 5.5V
	Control Pins	3.6			±1		V_I = 0V or V_{CC}
	Data Pins	3.6			−5		V_I = 0V
					1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current	0			±100	µA	0V ≤ V_I or V_O ≤ 5.5V
$I_{PU/PD}$	Power up/down 3-STATE Output Current	0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current	3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current	3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH16374).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	(Note 9)

Note 8: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
f_{max}	Maximum Clock Frequency	160			160		MHz
t_{PHL}	Propagation Delay	1.9		4.3	1.9	4.6	ns
t_{PLH}	CP to O_n	1.6		4.5	1.6	5.2	
t_{PZL}	Output Enable Time	1.3		4.4	1.3	5.0	ns
t_{PZH}		1.0		4.5	1.0	5.4	
t_{PLZ}	Output Disable Time	1.5		4.6	1.5	4.8	ns
t_{PHZ}		2.0		5.0	2.0	5.4	
t_S	Setup Time	1.8			2.0		ns
t_H	Hold Time	0.8			0.1		ns
t_W	Pulse Width	3.0			3.0		ns
t_{OSHL}	Output to Output Skew (Note 11)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

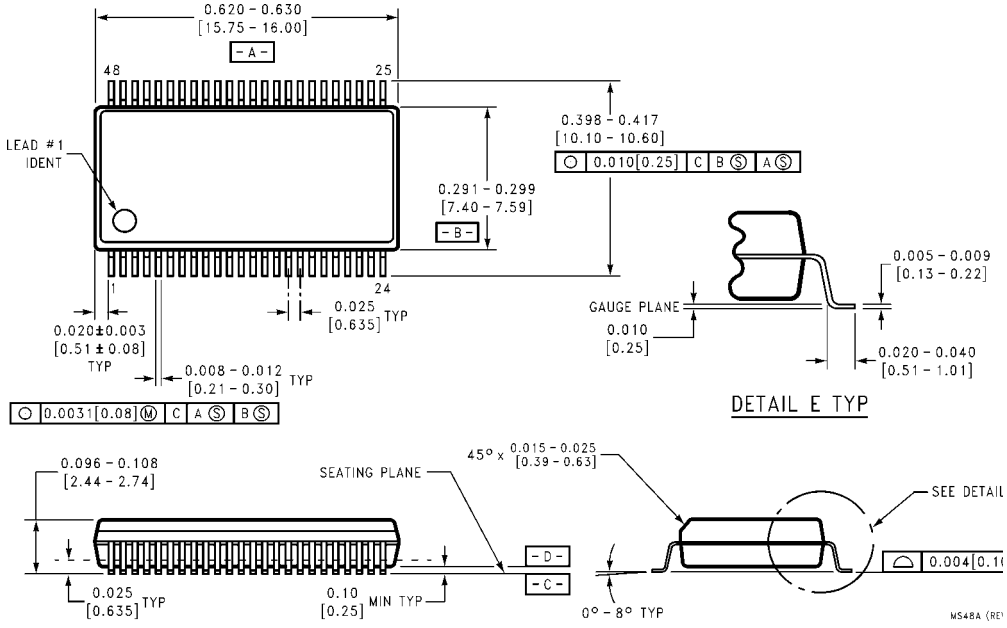
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 12)

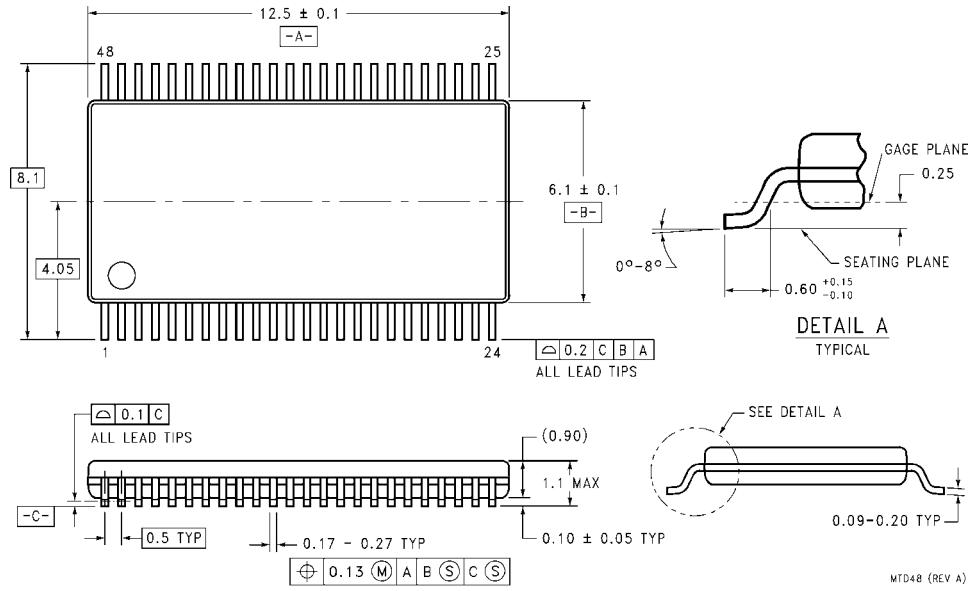
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

ADVANCE INFORMATION
October 1995

74LVT16500
3.3V ABT 18-Bit Universal Bus Transceivers with TRI-STATE® Outputs

General Description

The LVT16500 consist of eighteen universal bus transceivers combine D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and $\overline{\text{OEBA}}$), latch-enable (LEAB and LEBA), and clock ($\overline{\text{CLKAB}}$ and $\overline{\text{CLKBA}}$) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if $\overline{\text{CLKAB}}$ is held at a high or low logic level. If LEAB is low, the A bus data is stored in the latch/flip-flop on the high-to-low transition of $\overline{\text{CLKAB}}$. Output-enable OEAB is active-high. When OEAB is high, the outputs are active. When OEAB is low, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{\text{OEBA}}$, LEBA, and $\overline{\text{CLKBA}}$. The output enables are complementary (OEAB is active high and $\overline{\text{OEBA}}$ is active low).

The transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16500 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SSOP and TSSOP
- Functionally compatible with the 74 series 16500
- Latch-up performance exceeds 500 mA

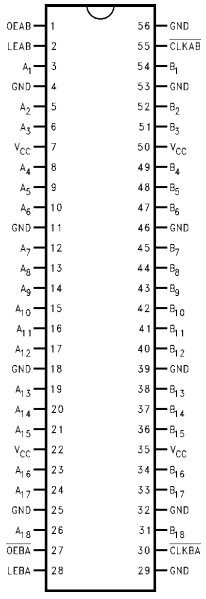
Pin Description

Pin Names	Description
A_0–A_{17}	Data Register A Inputs/TRI-STATE Outputs
B_0–B_{17}	Data Register B Inputs/TRI-STATE Outputs
$\overline{\text{CLKAB}}$, $\overline{\text{CLKBA}}$	Clock Pulse Inputs
LEAB, LEBA	Latch Enable Inputs
OEAB, $\overline{\text{OEBA}}$	Output Enable Inputs

	SSOP EIAJ	TSSOP
Order Number	74LVT16500MEA 74LVT16500MEAX	74LVT16500MTD 74LVT16500MTDX
NS Package Number	MS56A	MTD56

Connection Diagram

Pin Assignment for SSOP and TSSOP



TL/F/12447–1

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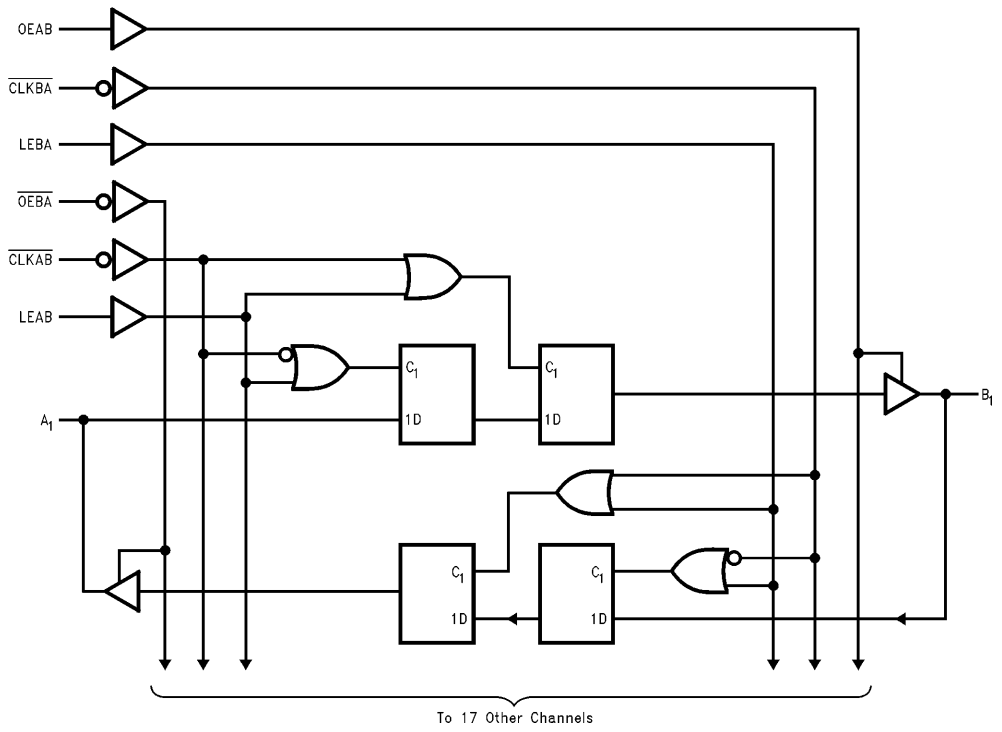
Logic Diagram



TL/F/12447–2

Function Table†

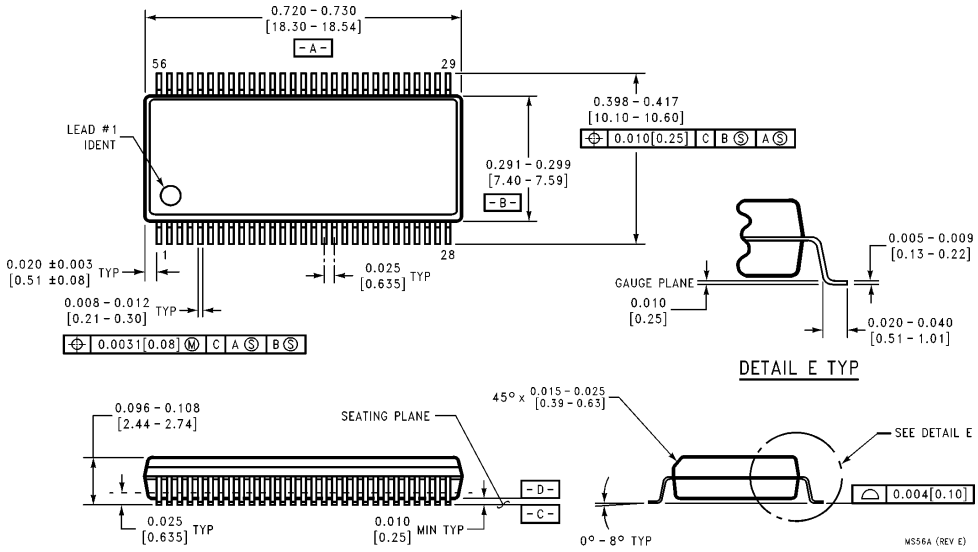
Inputs				Output
OEAB	LEAB	$\overline{\text{CLKAB}}$	A	B
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↓	L	L
H	L	↓	H	H
H	L	H	X	B_0‡
H	L	L	X	B_0§

† A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{\text{OEBA}}$, LEBA, and $\overline{\text{CLKBA}}$.

‡ Output level before the indicated steady-state input conditions were established.

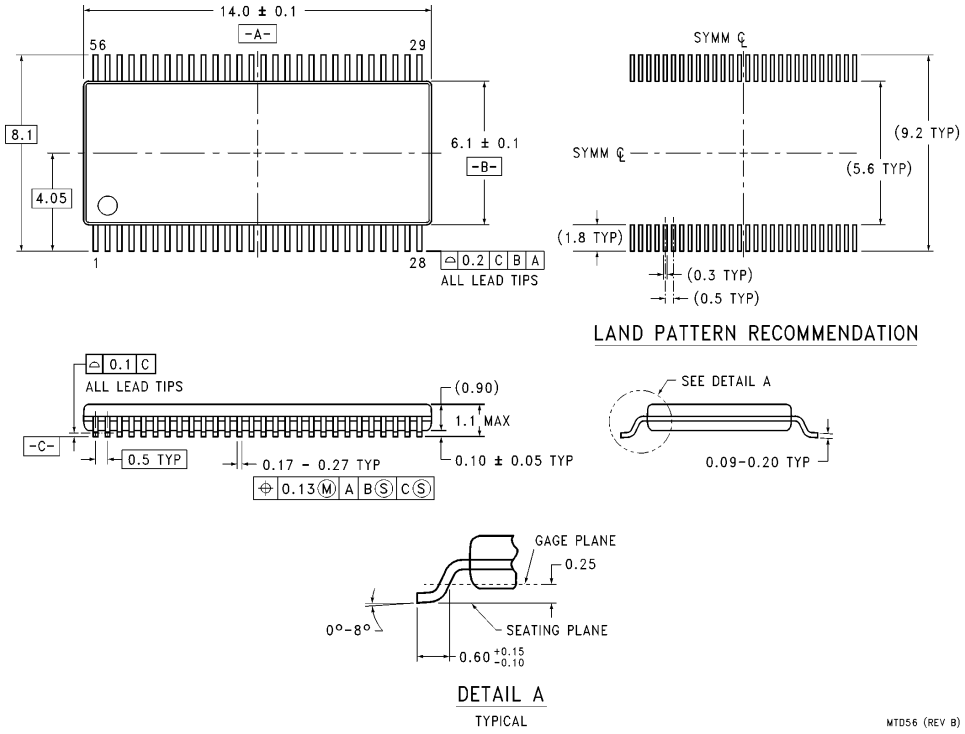
§ Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CLKAB}}$ was low before LEAB went low.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead (0.300″ Wide) Molded Shrink Small Outline Package, JEDEC
Order Number 74LVT16500MEA or 74LVT16500MEAX
NS Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Molded Thin Shrink Small Outline Package, JEDEC
Order Number 74LVT16500MTD or 74LVT16500MTDX
NS Package Number MTD56

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National Semiconductor

ADVANCE INFORMATION
October 1995

74LVT16543
3.3V ABT 16-Bit Registered Transceiver with TRI-STATE® Outputs

General Description

The 'LVT16543 16-bit transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. Each byte has separate control inputs, which can be shorted together for full 16-bit operation.

These transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16543 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

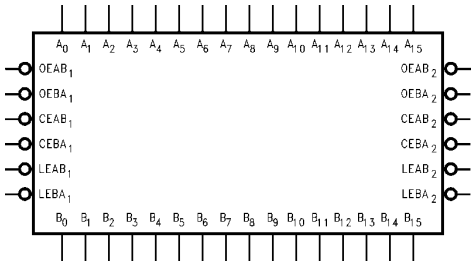
Features

- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SSOP and TSSOP
- Functionally compatible with the 74 series 16543
- Latch-up performance exceeds 500 mA

Pin Descriptions

Pin Names	Description
$\overline{OEAB}_n$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}_n$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}_n$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}_n$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}_n$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}_n$	B-to-A Latch Enable Input (Active LOW)
A_0–A_{15}	A-to-B Data Inputs or B-to-A TRI-STATE Outputs
B_0–B_{15}	B-to-A Data Inputs or A-to-B TRI-STATE Outputs

Logic Symbol

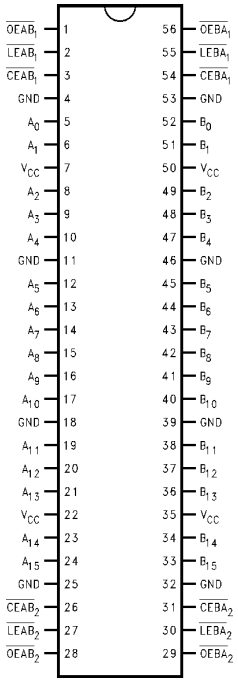


TL/F/12449–1

	SSOP EIAJ	TSSOP
Order Number	74LVT16543MEA 74LVT16543MEAX	74LVT16543MTD 74LVT16543MTDX
NS Package Number	MS56A	MTD56

Connection Diagram

Pin Assignment for SSOP and TSSOP



TL/F/12449–2

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Functional Description

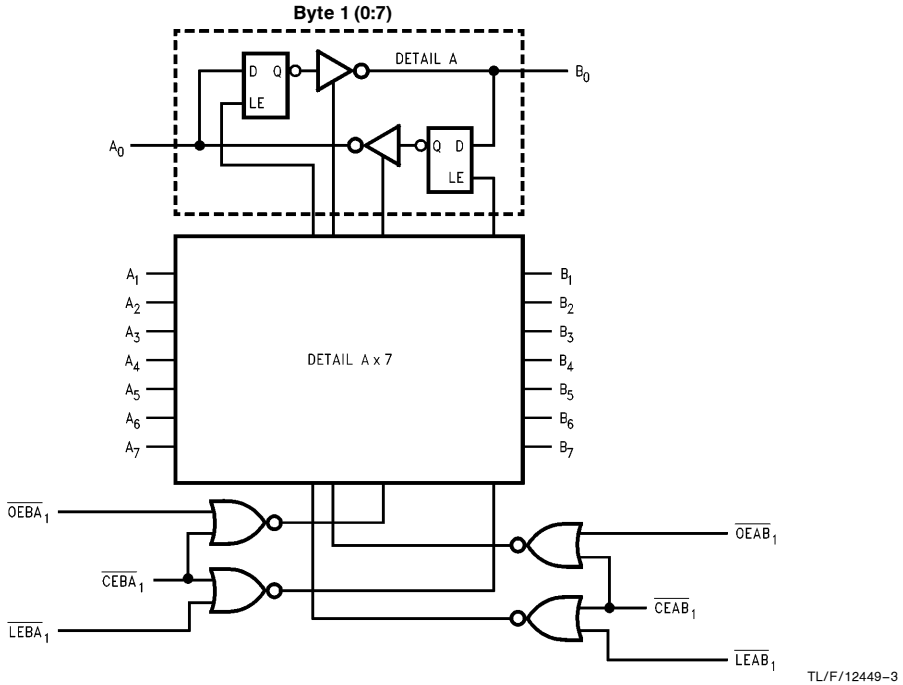
The ’LVT16543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable ($\overline{CEAB}$) input must be low in order to enter data from the A port or take data from the B port as indicated in the Data I/O Control Table. With $\overline{CEAB}$ low, a low signal on ($\overline{LEAB}$) input makes the A to B latches transparent; a subsequent low to high transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both low, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$. Each byte has separate control inputs, allowing the device to be used as two 8-bit transceivers or as one 16-bit transceiver.

Data I/O Control Table

Inputs			Latch Status (Byte n)	Output Buffers (Byte n)
$\overline{CEAB}_n$	$\overline{LEAB}_n$	$\overline{OEAB}_n$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$

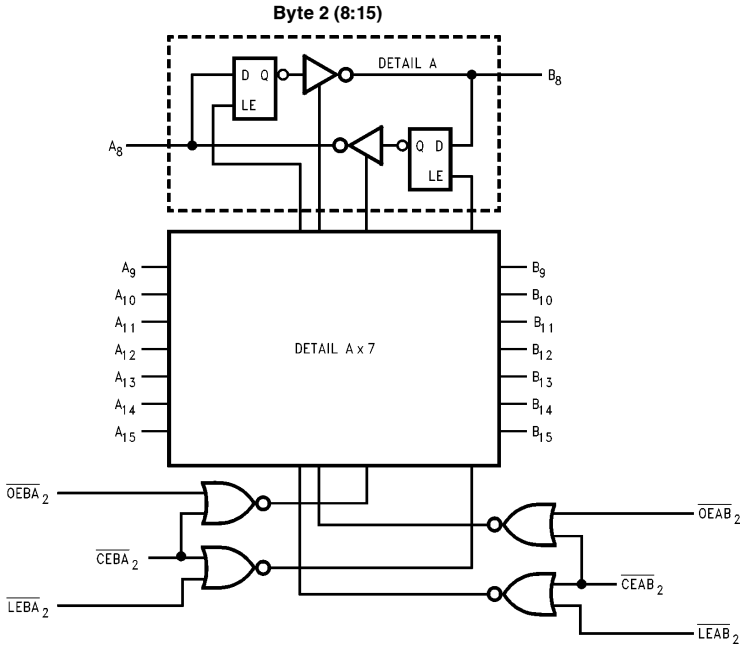
Logic Diagrams



TL/F/12449–3

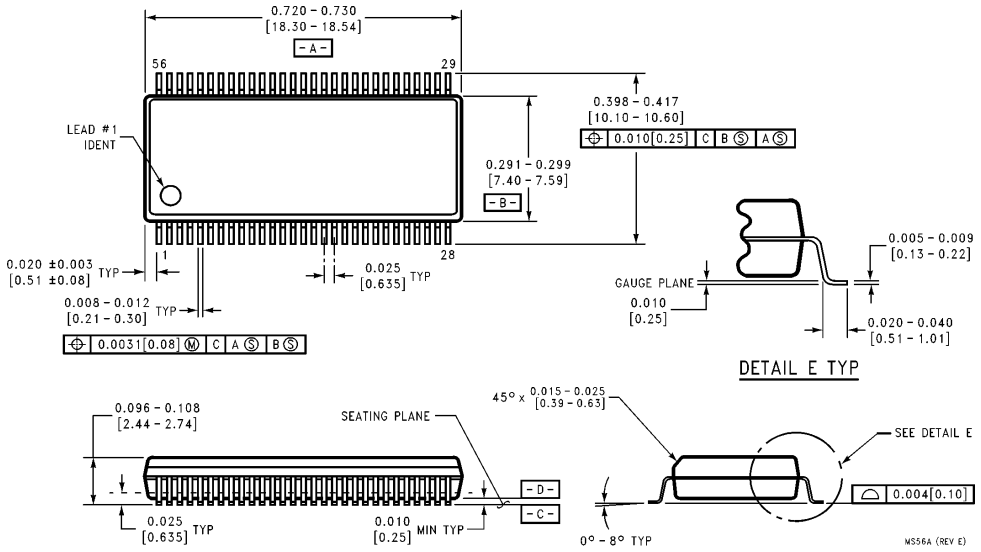
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Logic Diagrams (Continued)



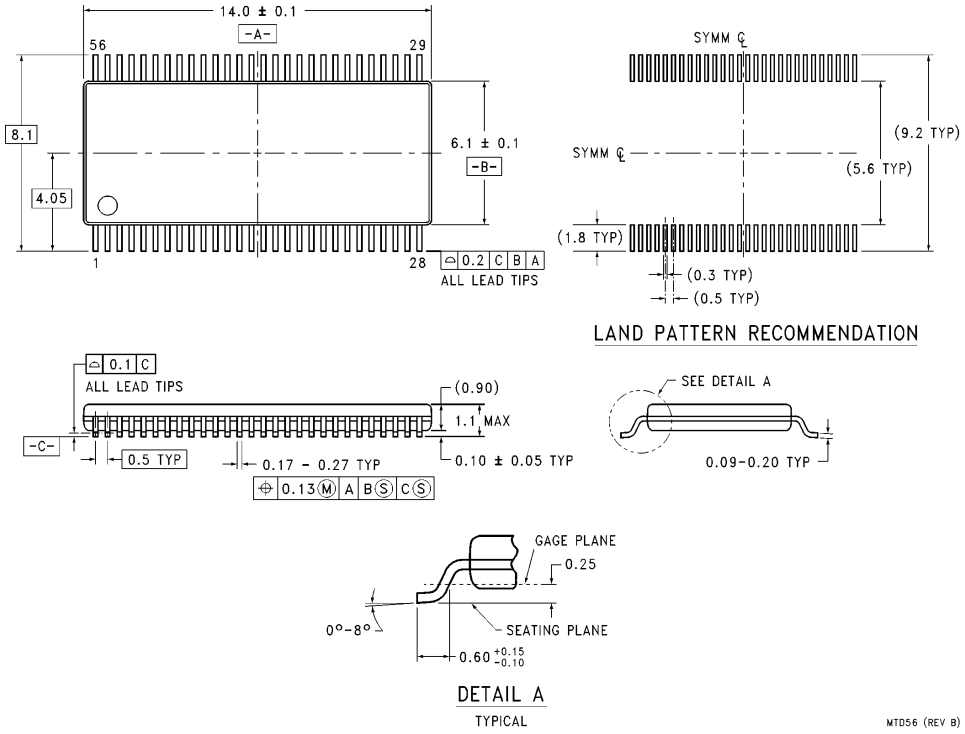
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead (0.300″ Wide) Molded Shrink Small Outline Package, JEDEC
Order Number 74LVT16543MEA or 74LVT16543MEAX
NS Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Molded Thin Shrink Small Outline Package, JEDEC
Order Number 74LVT16543MTD or 74LVT16543MTDX
NS Package Number MTD56

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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ADVANCE INFORMATION
December 1996

74LVT16646
3.3V ABT 16-Bit Transceiver/Register with TRI-STATE® Outputs

General Description

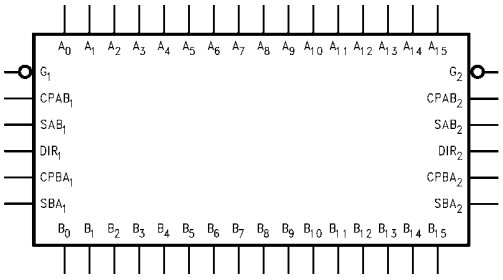
The LVT16646 contains sixteen non-inverting bidirectional registered bus transceivers providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition.

These transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16646 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SSOP and TSSOP
- Functionally compatible with the 74 series 16646
- Latch-up performance exceeds 500 mA

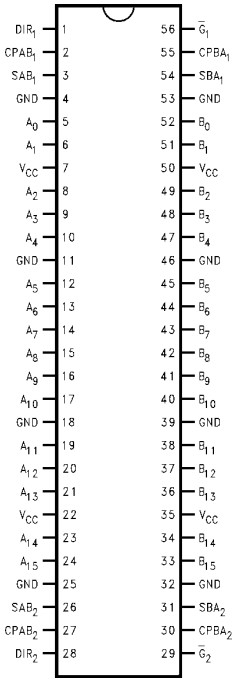
Logic Symbol



TL/F/12023–1

Connection Diagram

Pin Assignment for SSOP and TSSOP



TL/F/12023–2

	SSOP	TSSOP JEDEC
Order Number	74LVT16646MEA 74LVT16646MEAX	74LVT16646MTD 74LVT16646MTDX
See NS Package Number	MS56A	MTD56

Preliminary Data: National Semiconductor reserves the right to make changes at any time without notice.

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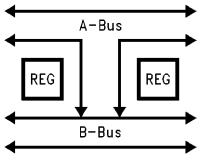
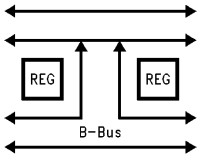
Real Time Transfer A-Bus to B-Bus



TL/F/12023–3

FIGURE 1

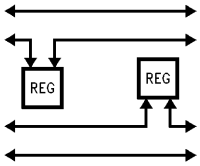
Real Time Transfer B-Bus to A-Bus



TL/F/12023–4

FIGURE 2

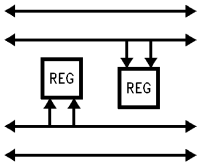
Storage from Bus to Register



TL/F/12023–5

FIGURE 3

Transfer from Register to Bus



TL/F/12023–6

FIGURE 4

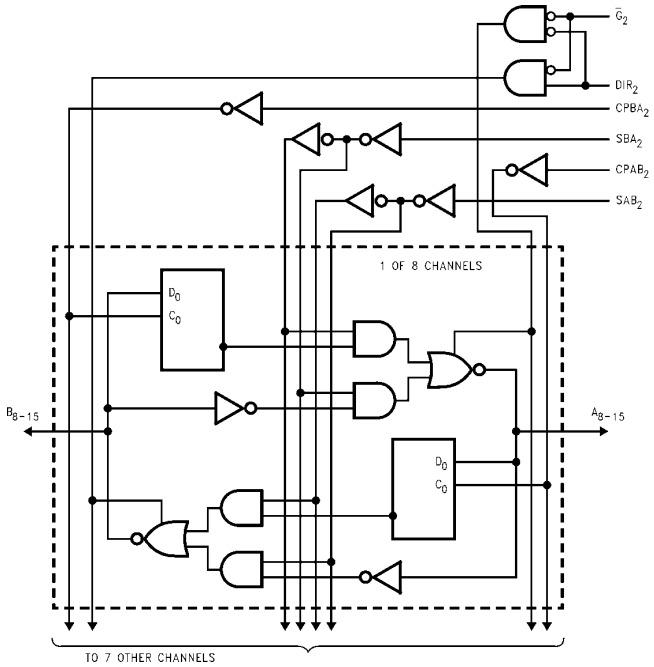
Truth Table (Note)

Inputs						Data I/O		Output Operation Mode
G_1	DIR_1	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_{0-7}	B_{0-7}	
H	X	H or L	H or L	X	X	Input	Input	Isolation
H	X	⌐	X	X	X			Clock An Data into A Register
H	X	X	⌐	X	X			Clock Bn Data Into B Register
L	H	X	X	L	X	Input	Output	An to Bn—Real Time (Transparent Mode)
L	H	⌐	X	L	X			Clock An Data to A Register
L	H	H or L	X	H	X			A Register to Bn (Stored Mode)
L	H	⌐	X	H	X			Clock An Data into A Register and Output to Bn
L	L	X	X	X	L	Output	Input	Bn to An—Real Time (Transparent Mode)
L	L	X	⌐	X	L			Clock Bn Data into B Register
L	L	X	H or L	X	H			B Register to An (Stored Mode)
L	L	X	⌐	X	H			Clock Bn into B Register and Output to An

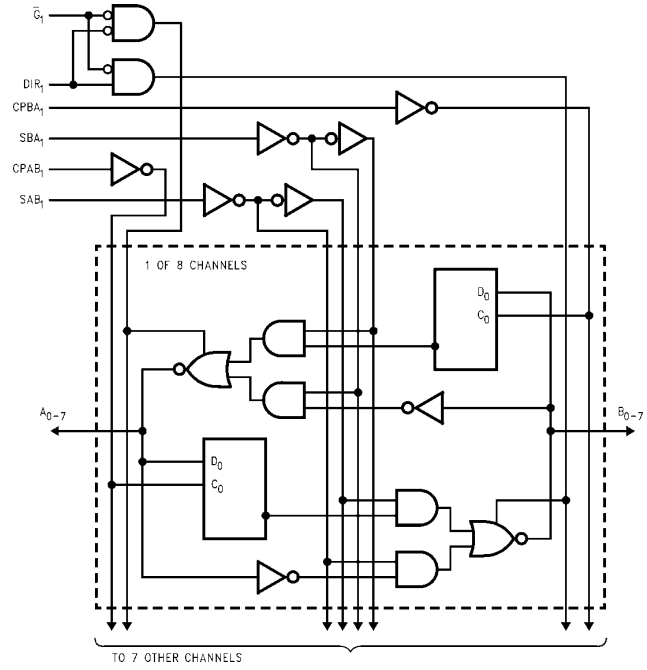
Note: The data output functions may be enabled or disabled by various signals at the G and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

H = HIGH Voltage Level X = Immaterial L = LOW Voltage Level ⌐ = LOW-to-HIGH Transition.

Logic Diagrams



TL/F/12023–7

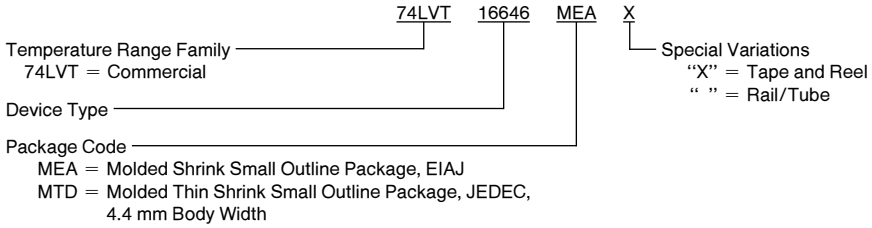


TL/F/12023–8

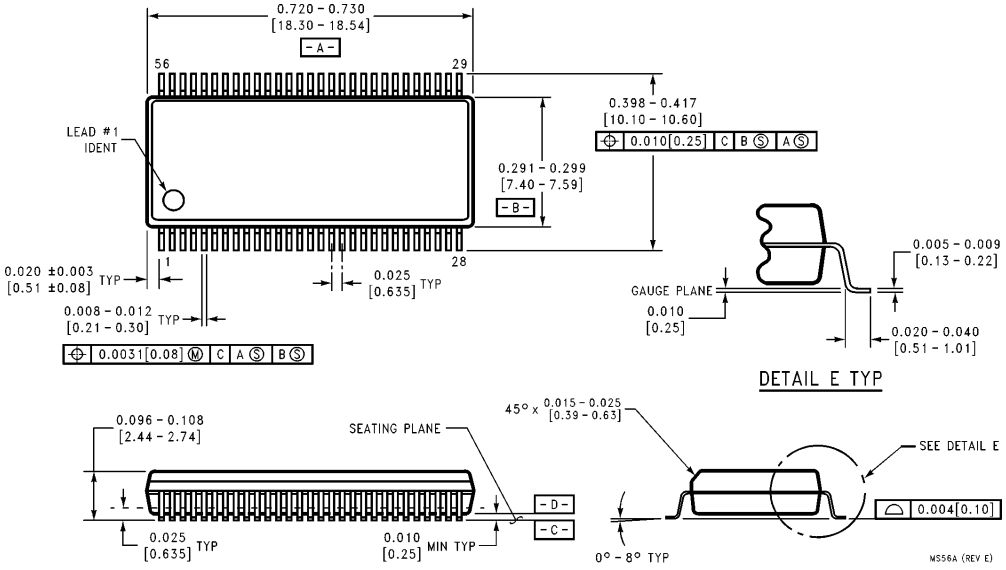
Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

74LVT16646 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

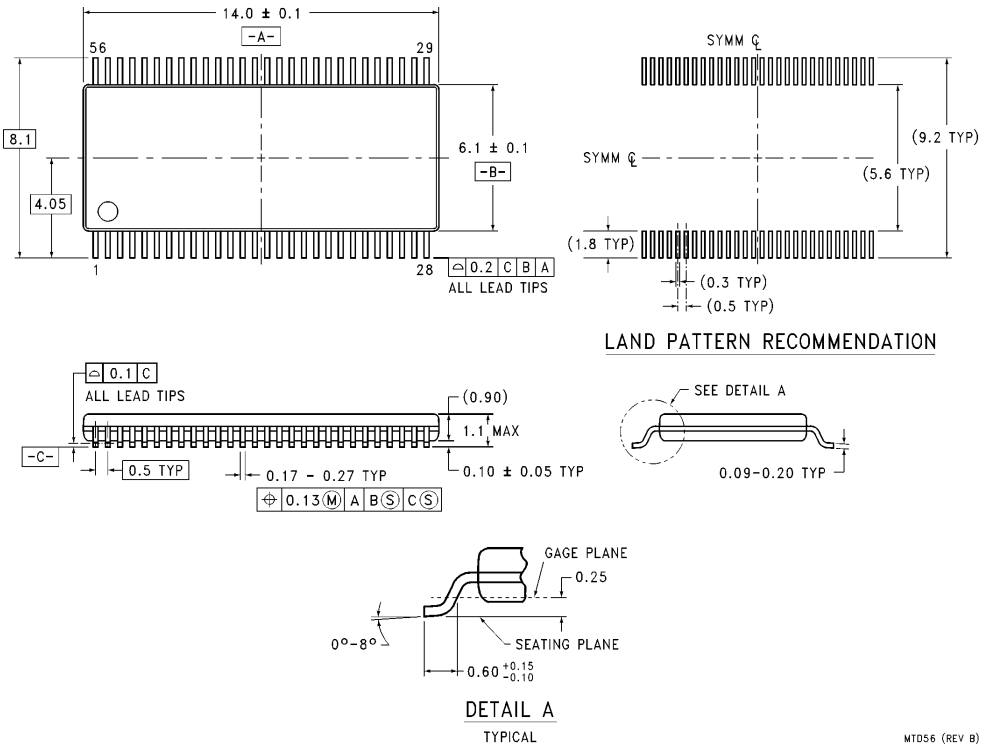


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Molded Shrink Small Outline Package, JEDEC, EIAJ
Order Number 74LVT16646MEA or 74LVT16646MEAX
NS Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Molded Thin Shrink Small Outline Package, JEDEC, 6.1 mm Body Width
Order Number 74LVT16646MTD or 74LVT16646MTDX
NS Package Number MTD56

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ADVANCE INFORMATION
October 1995

74LVT16652
3.3V ABT 16-Bit Transceiver/Register with TRI-STATE® Outputs

General Description

The LVT16652 consists of sixteen bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function.

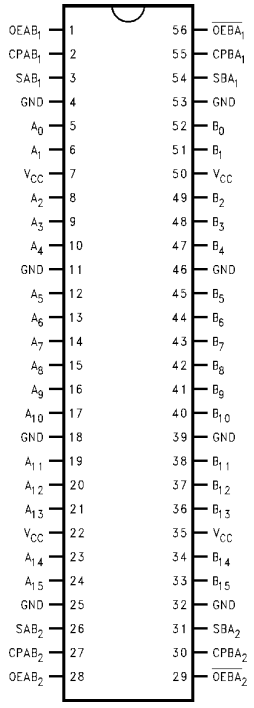
The transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT16652 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SSOP and TSSOP
- Functionally compatible with the 74 series 16652
- Latch-up performance exceeds 500 mA

Connection Diagram

Pin Assignment for SSOP and TSSOP



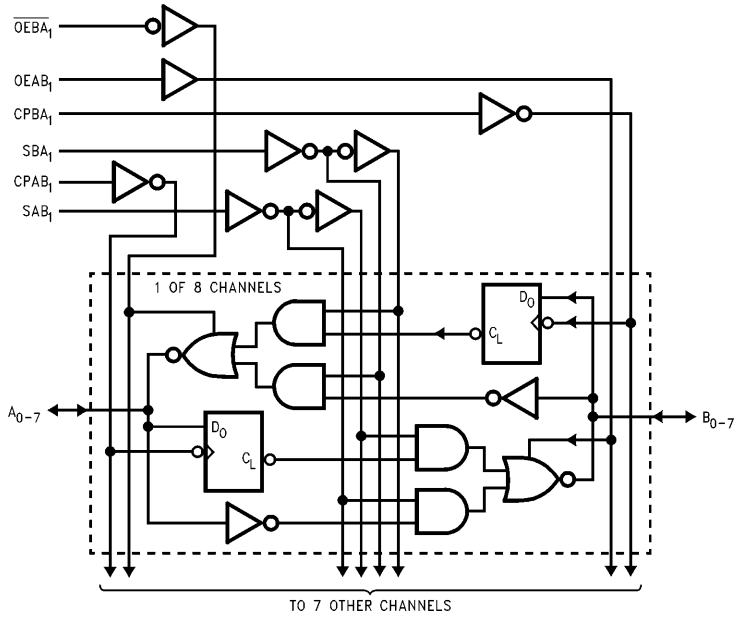
TL/F/12024–1

Pin Names	Description
A_0–A_{16}	Data Register A Inputs/ TRI-STATE Outputs
B_0–B_{16}	Data Register B Inputs/ TRI-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
$OEAB_n$, $\overline{OEBA}_n$	Output Enable Inputs

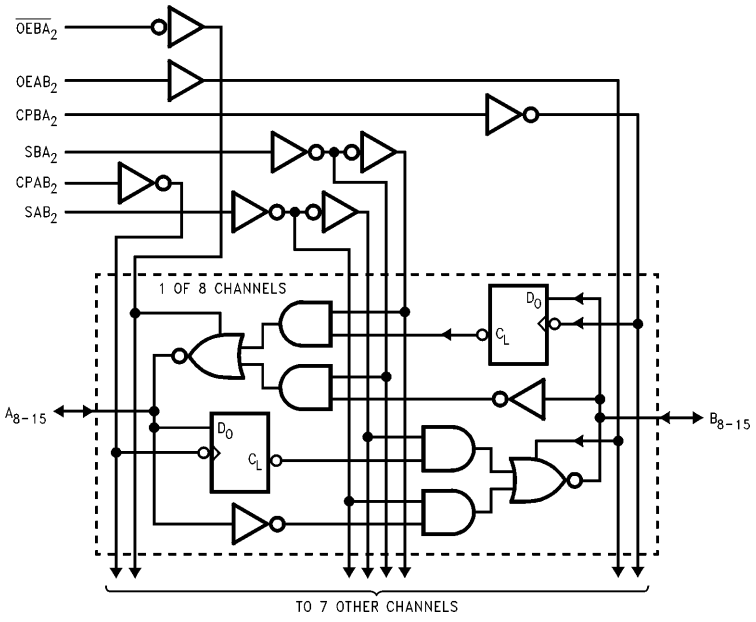
	SSOP EIAJ	TSSOP JEDEC
Order Number	74LVT16652MEA 74LVT16652MEAX	74LVT16652MTD 74LVT16652MTDX
NS Package Number	MS56A	MTD56

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Logic Diagrams



TL/F/12024–2



TL/F/12024–3

Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB_n, SBA_n) controls can multiplex stored and real-time.

The examples in *Figure 1* demonstrate the four fundamental bus-management functions that can be performed with the LVT16652.

Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs ($CPAB_n$, $CPBA_n$) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling $OEAB_n$ and $\overline{OEBA}_n$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

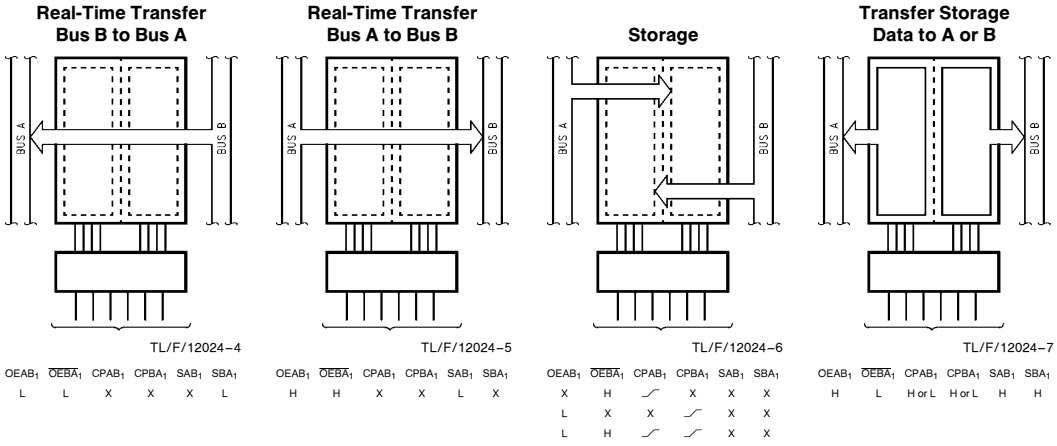


FIGURE 1

Truth Table (Note)

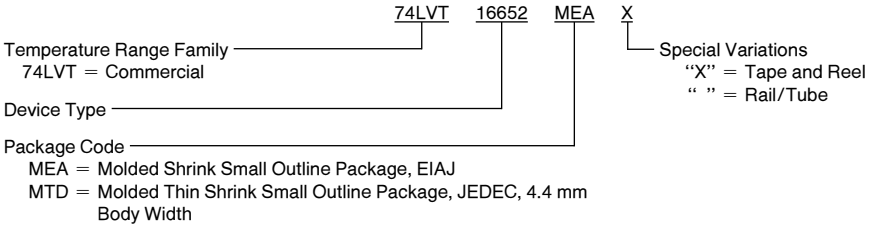
Inputs						Inputs/Outputs		Operating Mode
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial ⌐ = LOW to HIGH Clock Transition

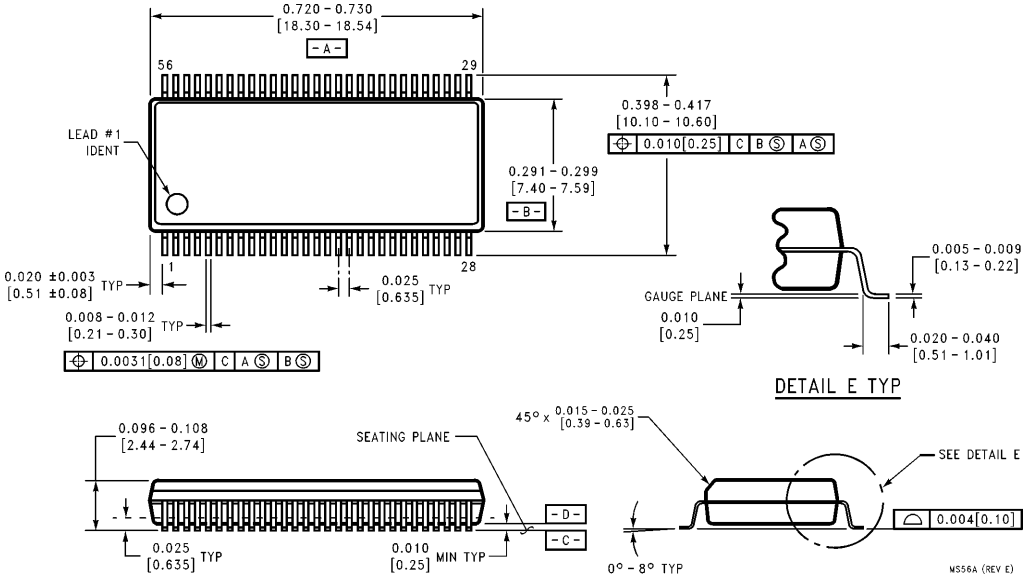
Note: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW to HIGH transition on the clock inputs. This also applies to data I/O (A and B: 8–15) and #2 control pins.

74LVT16652 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

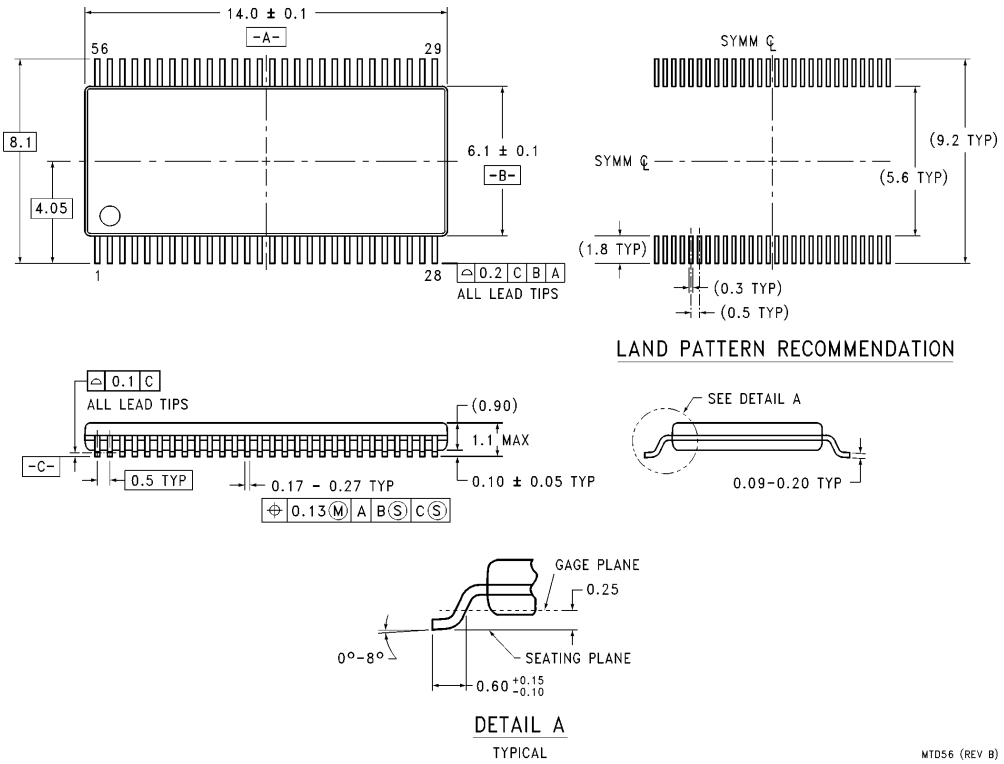


Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Molded Shrink Small Outline Package, EIAJ
Order Number 74LVT16652MEA or 74LVT16652MEAX
NS Package Number MS56A

Physical Dimensions millimeters (Continued)



56-Lead Molded Thin Shrink Small Outline Package, JEDEC, 6.1 mm Body Width
Order Number 74LVT16652MTD or 74LVT16652MTDX
NS Package Number MTD56

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised August 1999

74LVT2240 • 74LVTH2240
Low Voltage Inverting Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVT2240 and LVTH2240 are inverting octal buffers and line drivers designed to be employed as memory address drivers, clock drivers and bus oriented transmitters or receivers which provides improved PC board density. The equivalent 25Ω-Series resistors helps reduce output overshoot and undershoot.

The LVTH2240 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These inverting octal buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT2240 and LVTH2240 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

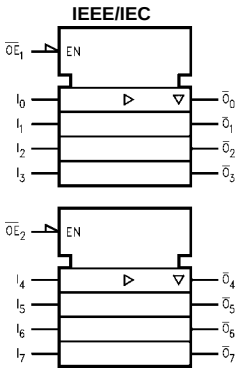
- Input and output interface capability to systems at 5V V_{CC}
- Equivalent 25Ω-Series resistors on outputs
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH2240), also available without bushold feature (74LVT2240).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −12 mA/+12 mA
- Latch-up performance exceeds 500 mA

Ordering Code:

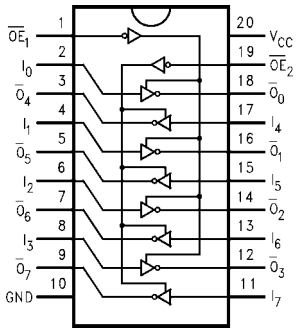
Order Number	Package Number	Package Description
74LVT2240WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVT2240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT2240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH2240WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVTH2240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH2240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−12	mA
I_{OL}	LOW-Level Output Current		12	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6			0.8		
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			3.0	2.0			V	I_{OH} = −12 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			3.0			0.8	V	I_{OL} = 12 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75			µA	V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500			µA	(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6			−5	µA	V_I = 0V
						1	µA	V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	0V ≤ V_I or V_O ≤ 5.5V
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V
I_{OZH+}	3-STATE Output Leakage Current		3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH2240).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each, input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.0		4.0	1.0	4.8	ns
t_{PHL}		1.0		4.1	1.0	4.4	
t_{PZH}	Output Enable Time	1.0		5.0	1.0	6.0	ns
t_{PZL}		1.1		5.0	1.1	5.6	
t_{PHZ}	Output Disable Time	1.9		4.8	1.9	5.5	ns
t_{PLZ}		1.8		4.5	1.8	4.5	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

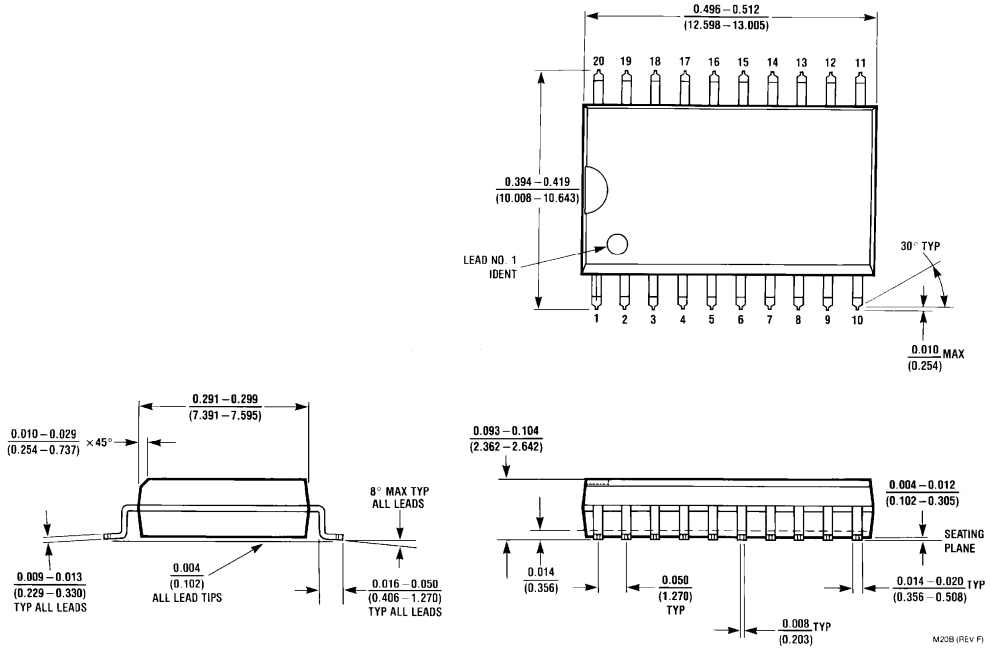
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

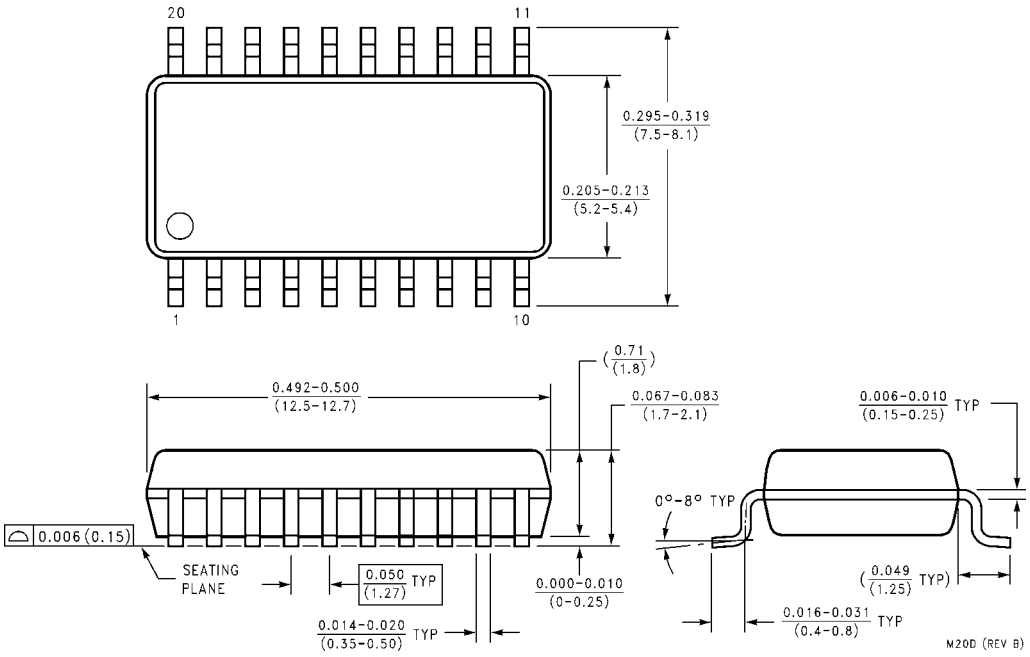
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	3	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

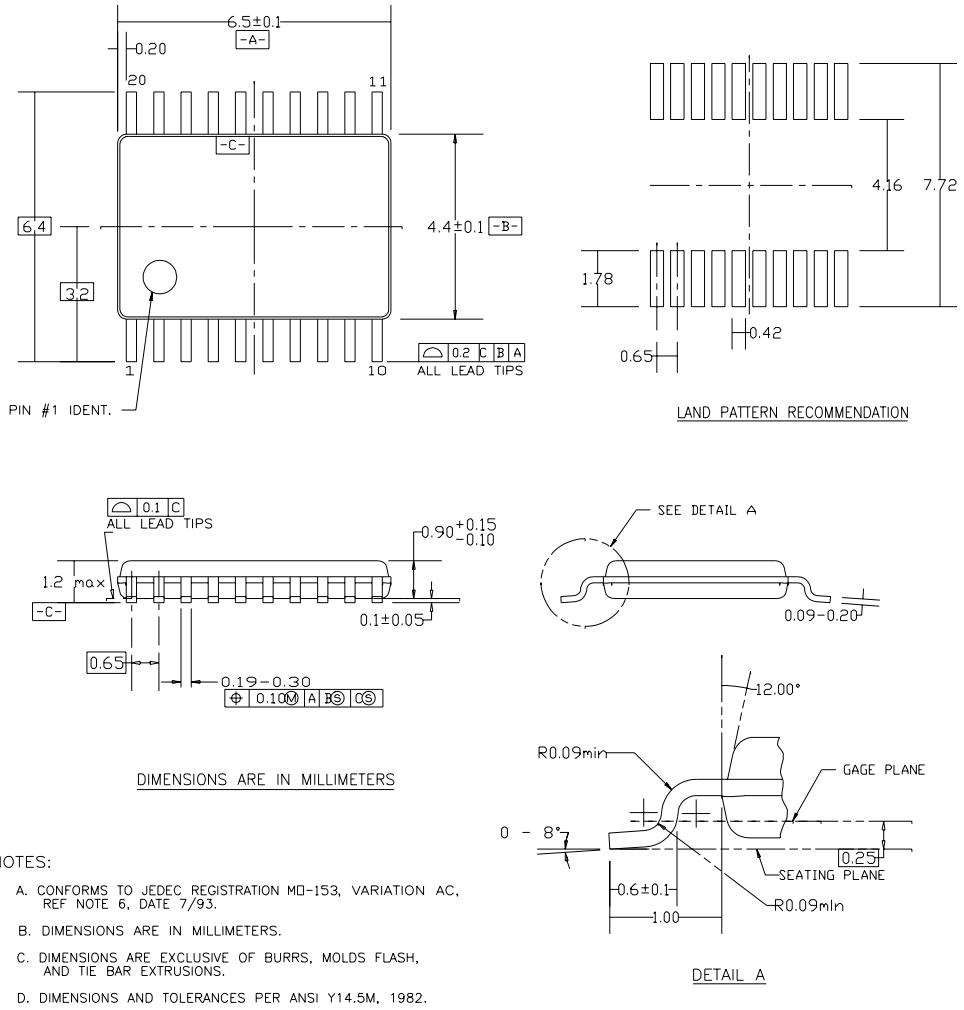


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised August 1999

74LVT2244 • 74LVTH2244
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVT2244 and LVTH2244 are octal buffers and line drivers designed to be employed as memory address drivers, clock drivers and bus oriented transmitters or receivers which provides improved PC board density. The equivalent 25Ω-Series resistors helps reduce output overshoot and undershoot.

The LVTH2244 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT2244 and LVTH2244 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

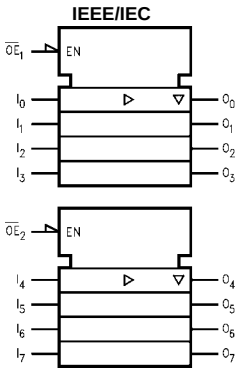
- Input and output interface capability to systems at 5V V_{CC}
- Equivalent 25Ω-Series resistors on outputs
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH2244), also available without bushold feature (74LVT2244).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −12 mA/+12 mA
- Latch-up performance exceeds 500 mA

Ordering Code:

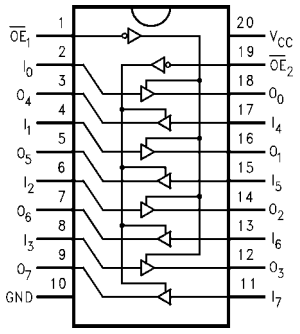
Order Number	Package Number	Package Description
74LVT2244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVT2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT2244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH2244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVTH2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH2244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	L
L	H	H
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	–0.5 to +4.6		V
V_I	DC Input Voltage	–0.5 to +7.0		V
V_O	DC Output Voltage	–0.5 to +7.0	Output in 3-STATE	V
		–0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	–65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		–12	mA
I_{OL}	LOW-Level Output Current		12	
T_A	Free-Air Operating Temperature	–40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = –40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			–1.2	V	I_I = –18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} – 0.2			V	I_{OH} = –100 µA
			3.0	2.0			V	I_{OH} = –12 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			3.0			0.8	V	I_{OL} = 12 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				–75			µA	V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				–500			µA	(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6			–5	µA	V_I = 0V
						1	µA	V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	0V ≤ V_I or V_O ≤ 5.5V
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V
								V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			–5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V
I_{OZH+}	3-STATE Output Leakage Current		3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH2244).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each, input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.0		4.4	1.0	5.3	ns
t_{PHL}		1.0		4.1	1.0	4.4	
t_{PZH}	Output Enable Time	1.0		5.9	1.0	7.7	ns
t_{PZL}		1.1		5.5	1.1	6.2	
t_{PHZ}	Output Disable Time	1.9		6.1	1.9	6.8	ns
t_{PLZ}		1.8		4.5	1.8	4.5	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

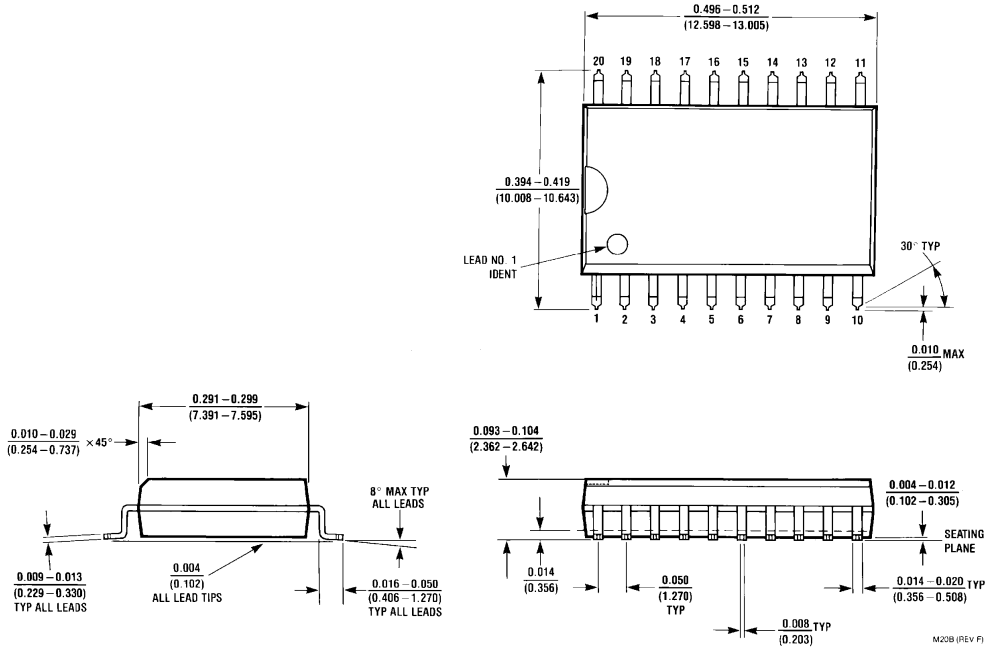
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

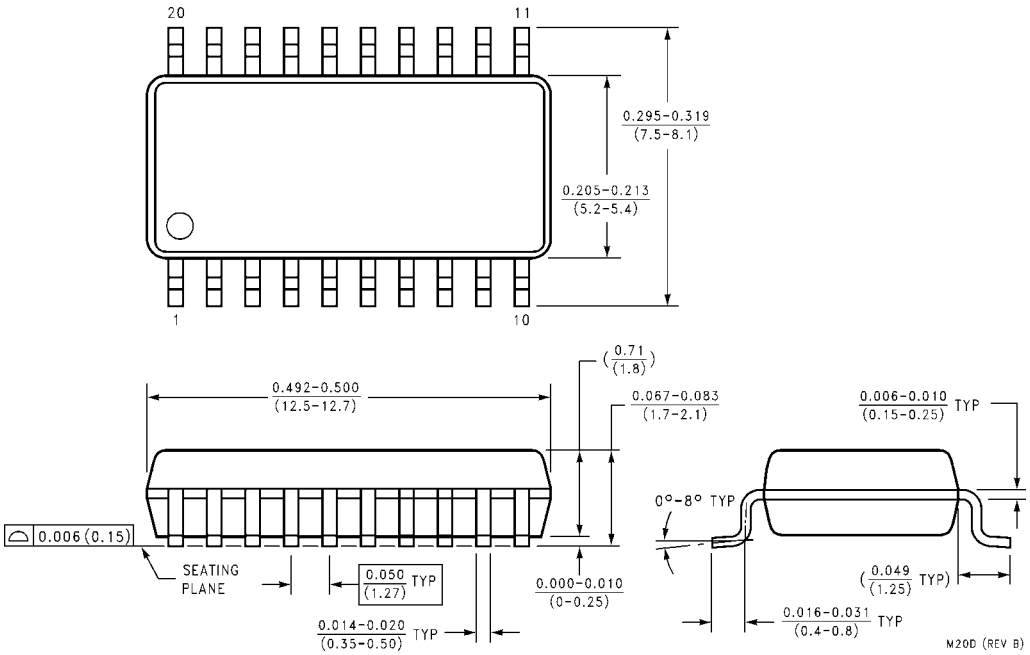
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	3	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

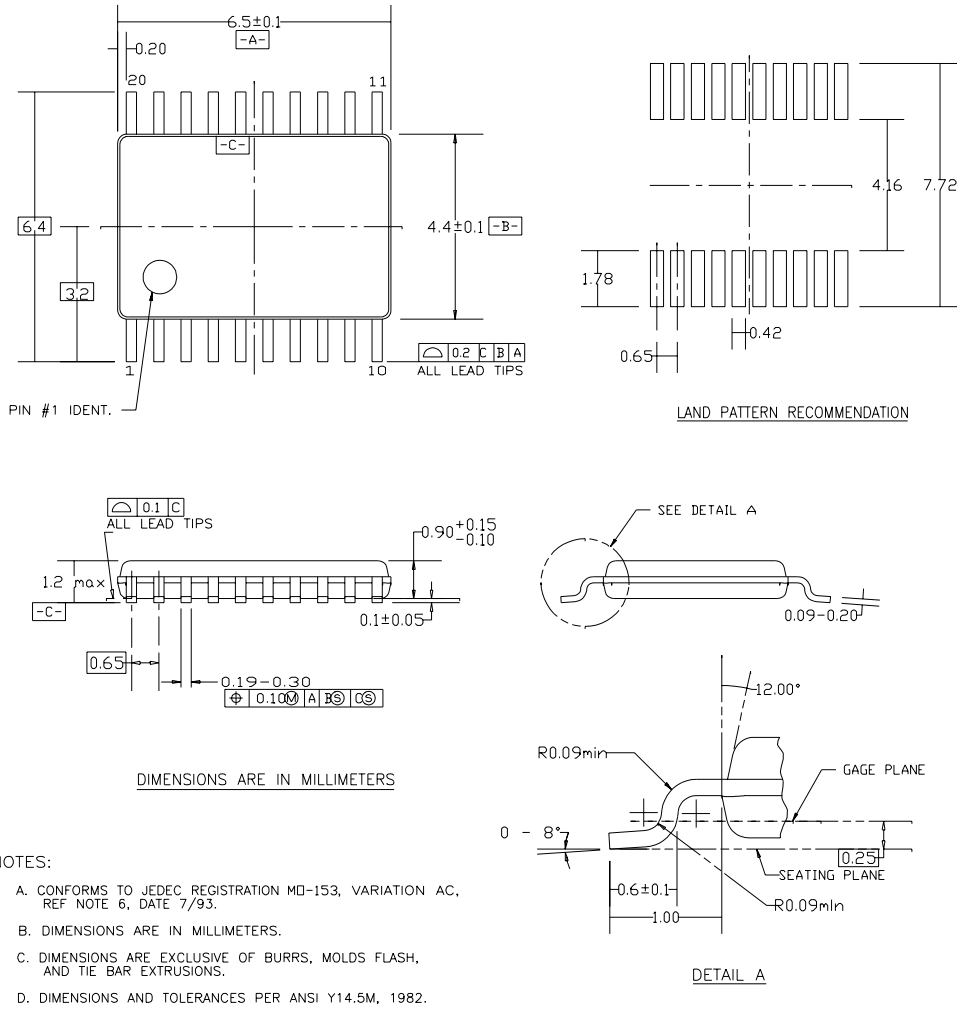


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1999
Revised January 2000

74LVT2245 • 74LVTH2245
Low Voltage Octal Bidirectional Transceiver with 3-STATE Inputs/Outputs and 25Ω Series Resistors in the B Port Outputs

General Description

The LVT2245 and LVTH2245 contain eight non-inverting bidirectional buffers with 3-STATE outputs and are intended for bus-oriented applications. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a high impedance state. The equivalent 25Ω-series resistor in the B Port helps reduce output overshoot and undershoot.

The LVTH2245 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These transceivers are designed for low voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT2245 and LVTH2245 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

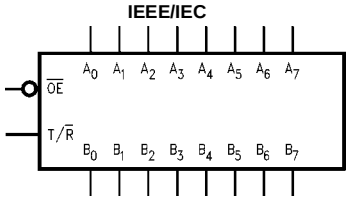
- Input and output interface capability to systems at 5V V_{CC}
- Equivalent 25Ω series resistor on B Port outputs
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH2245), also available without bushold feature (74LVT2245)
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –12 mA/+12 mA on B Port, –32 mA/+64 mA on A Port
- Latch-up performance exceeds 500 mA

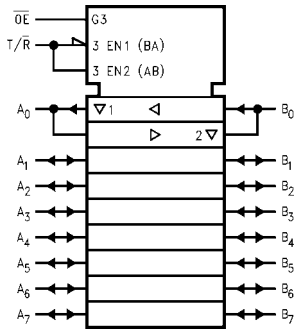
Ordering Code:

Order Number	Package Number	Package Description
74LVT2245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVT2245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVT2245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVT2245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH2245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH2245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVTH2245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVTH2245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

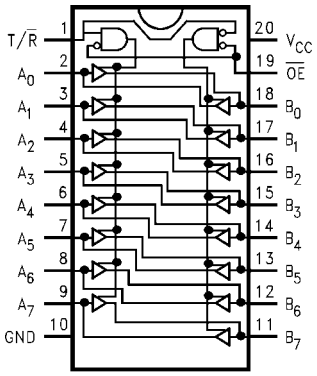
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage		2.7	3.6	V
V_I	Input Voltage		0	5.5	V
I_{OH}	HIGH-Level Output Current	A Port		−32	mA
		B Port		−12	
I_{OL}	LOW-Level Output Current	A Port		64	mA
		B Port		12	
T_A	Free Air Operating Temperature		−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units	Conditions
				Min	Max		
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage	A Port	2.7	2.4		V	$I_{OH} = -8$ mA
			3.0	2.0			$I_{OH} = -32$ mA
		B Port	3.0	2.0		V	$I_{OH} = -12$ mA
			2.7–3.6	$V_{CC}-0.2$		V	$I_{OH} = -100$ µA
V_{OL}	Output LOW Voltage	A Port	2.7		0.5	V	$I_{OL} = 24$ mA
			3.0		0.4		$I_{OL} = 16$ mA
			3.0		0.5		$I_{OL} = 32$ mA
			3.0		0.55		$I_{OL} = 64$ mA
		B Port	3.0		0.8	V	$I_{OL} = 12$ mA
			2.7		0.2	V	$I_{OL} = 100$ µA
$I_{I(HOLD)}$ (Note 3)	Bushold Input Minimum Drive		3.0	75		µA	$V_I = 0.8V$
				−75			$V_I = 2.0V$
$I_{I(OD)}$ (Note 3)	Bushold Input Over-Drive Current to Change State		3.0	500		µA	(Note 4)
				−500			(Note 5)
I_I	Input Current		3.6		10	µA	$V_I = 5.5V$
		Control Pins	3.6		±1		$V_I = 0V$ or V_{CC}
		Data Pins	3.6		−5		$V_I = 0V$
					1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0–1.5V		±100	µA	$V_O = 0.5V$ to $3.0V$ V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	$V_O = 0.5V$
I_{OZL} (Note 3)	3-STATE Output Leakage Current		3.6		−5	µA	$V_O = 0.0V$
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	$V_O = 3.0V$
I_{OZH} (Note 3)	3-STATE Output Leakage Current		3.6		5	µA	$V_O = 3.6V$
$I_{OZH}+$	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs High
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs Low
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 6)		3.6		0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: Applies to Bushold versions only (74LVTH2245).

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay Data to B Port Output	1.2	4.4	1.2	5.1	ns
t_{PHL}		1.2	4.4	1.2	5.1	
t_{PLH}	Propagation Delay Data to A Port Output	1.2	3.6	1.2	4.0	ns
t_{PHL}		1.2	3.5	1.2	4.0	
t_{PZH}	Output Enable Time for B Port Output	1.3	6.2	1.3	7.3	ns
t_{PZL}		1.7	6.2	1.7	7.3	
t_{PZH}	Output Enable Time for A Port Output	1.3	5.5	1.3	7.1	ns
t_{PZL}		1.7	5.7	1.7	6.7	
t_{PHZ}	Output Disable Time for B Port Output	2.0	5.9	2.0	6.5	ns
t_{PLZ}		2.0	5.4	2.0	5.7	
t_{PHZ}	Output Disable Time for A Port Output	2.0	5.9	2.0	6.5	ns
t_{PLZ}		2.0	5.0	2.0	5.1	
t_{OSHL}	A Port Output to Output Skew		1.0		1.0	ns
t_{OSLH}	(Note 9)					
t_{OSHL}	B Port Output to Output Skew		1.0		1.0	ns
t_{OSLH}	(Note 9)					

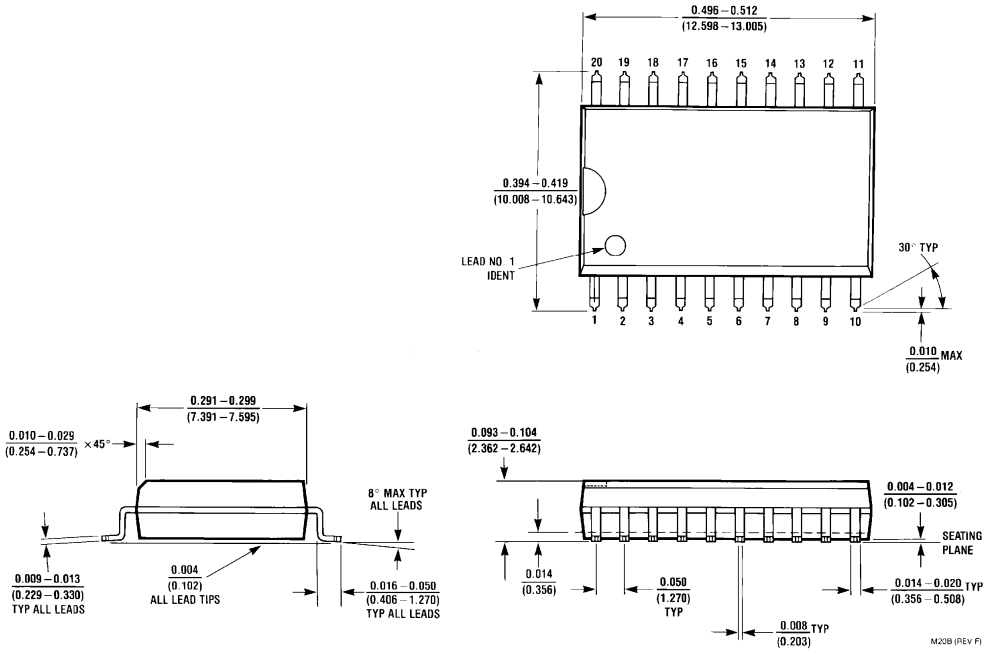
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 10)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

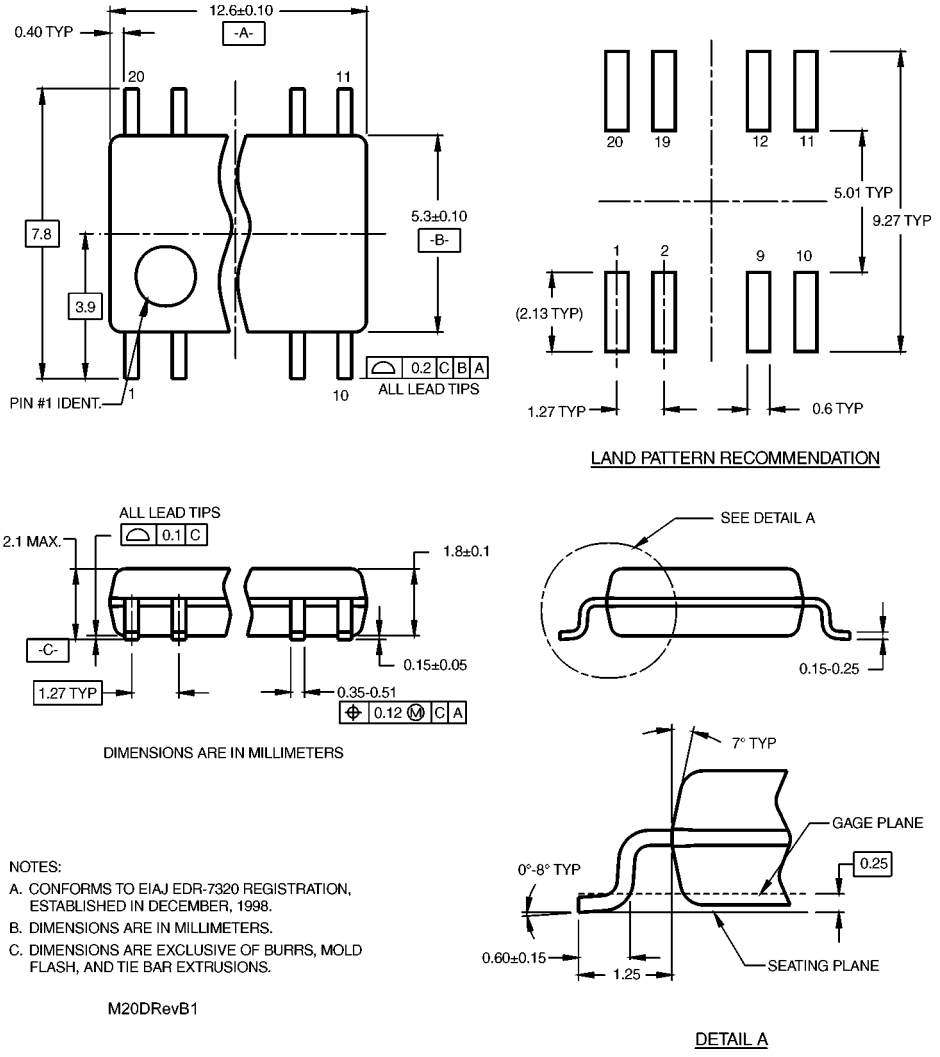
Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

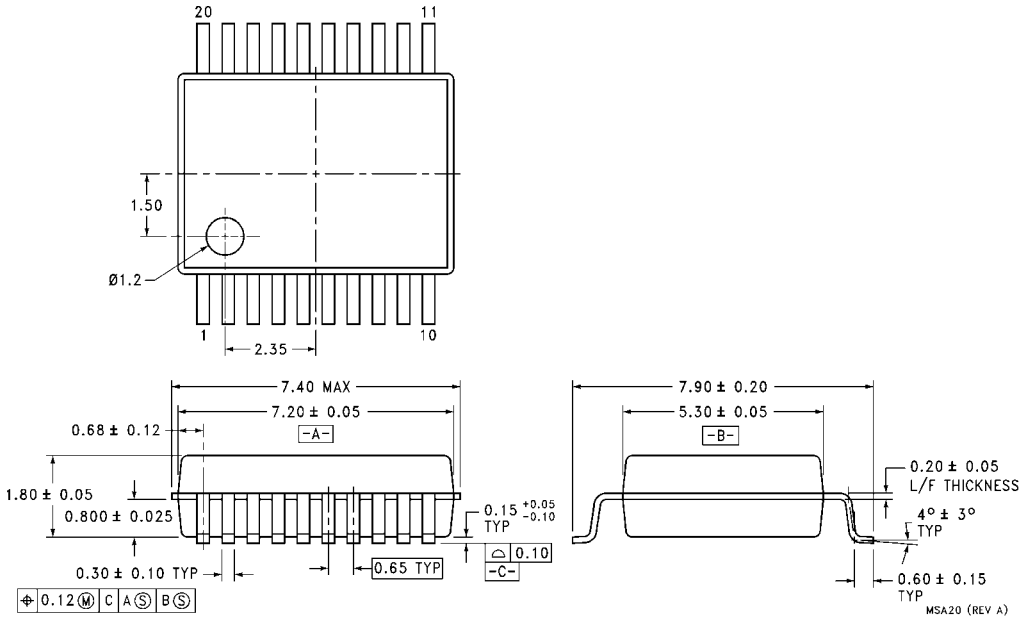
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

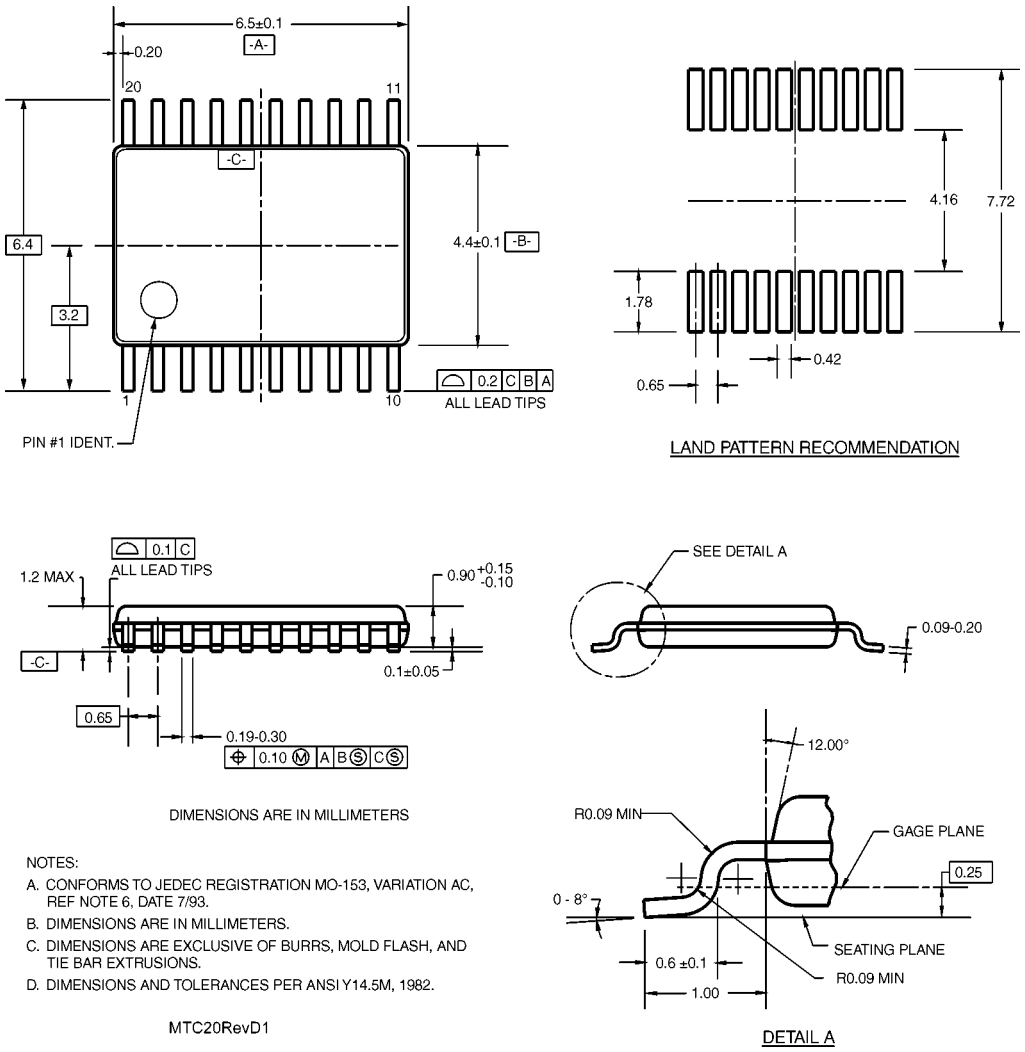
20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised August 1999

74LVT240 • 74LVTH240
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVT240 and LVTH240 are inverting octal buffers and line drivers designed to be employed as memory address drivers, clock drivers and bus oriented transmitters or receivers which provides improved PC board density.

The LVTH240 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT240 and LVTH240 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

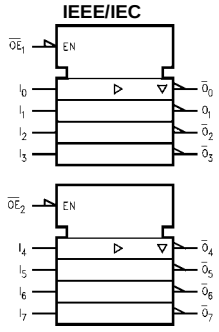
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH240), also available without bushold feature (74LVT240).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 240
- Latch-up performance exceeds 500 mA

Ordering Code:

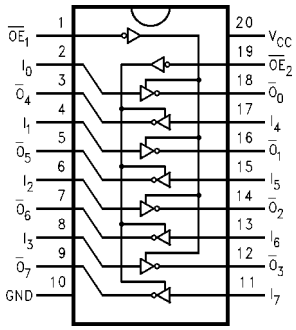
Order Number	Package Number	Package Description
74LVT240WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVT240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT240MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVT240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH240WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVTH240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH240MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVTH240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	3-STATE Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	mA
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC}−0.2			V	I_{OH} = −100 µA
			2.7	2.4			V	I_{OH} = −8 mA
			3.0	2.0			V	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5	V	I_{OL} = 24 mA
			3.0			0.4	V	I_{OL} = 16 mA
			3.0			0.5	V	I_{OL} = 32 mA
			3.0			0.55	V	I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75			µA	V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500			µA	(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6			−5	µA	V_I = 0V
						1	µA	V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH240).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		–0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.1		3.8	1.1	4.6	ns
t_{PHL}		1.3		4.0	1.3	4.2	
t_{PZH}	Output Enable Time	1.1		4.6	1.1	5.6	ns
t_{PZL}		1.4		4.4	1.4	5.1	
t_{PHZ}	Output Disable Time	2.0		4.5	2.0	4.7	ns
t_{PLZ}		1.8		4.3	1.8	4.3	
t_{OSHL}	Output to Output Skew (Note 11)			1.0		1.0	ns
t_{OSLH}							

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

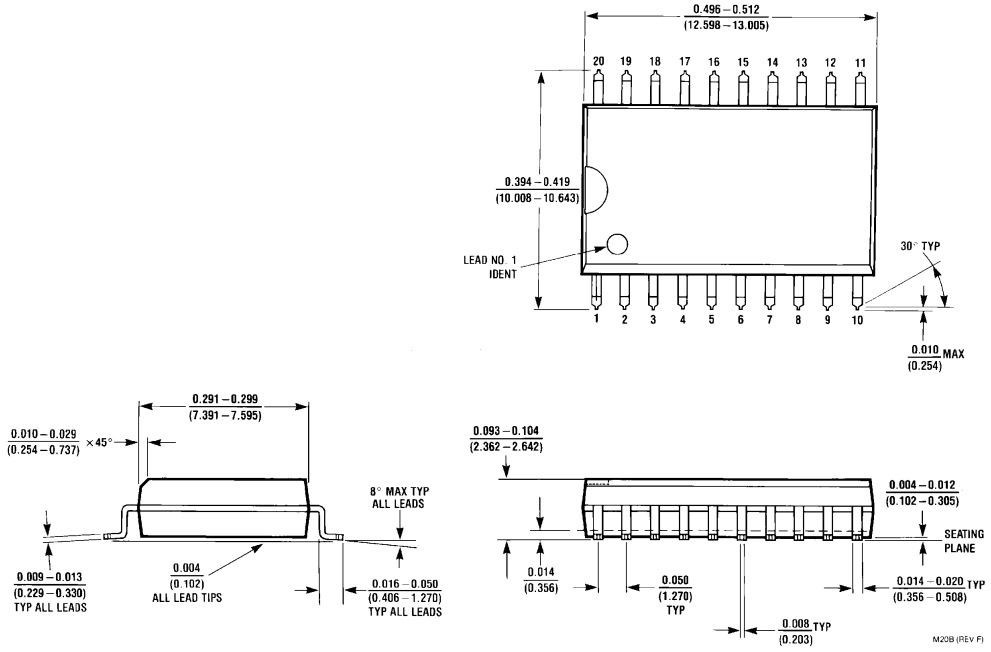
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

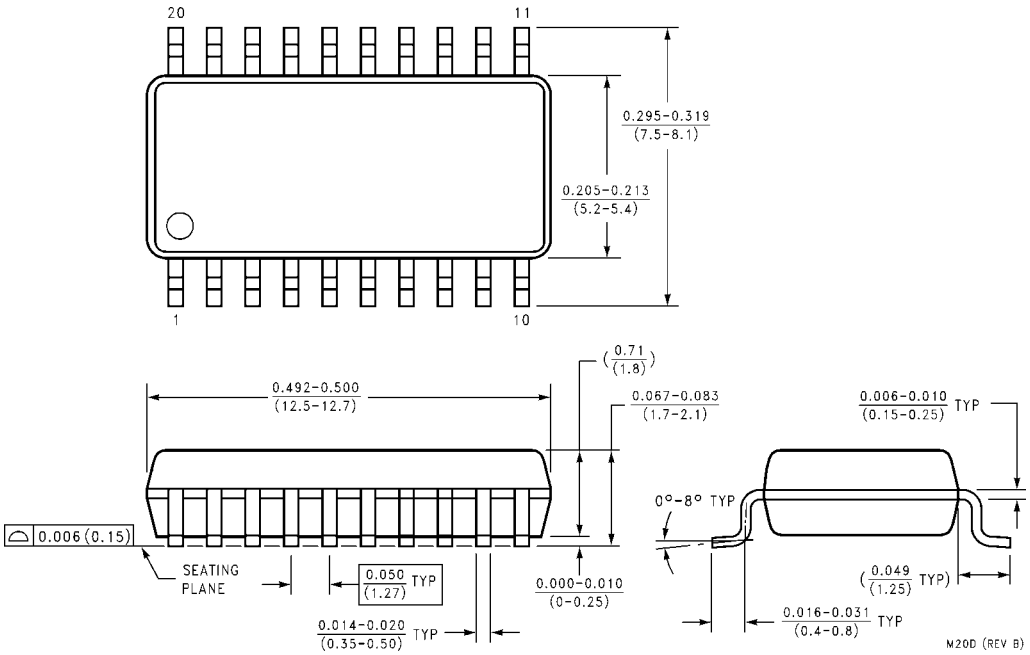
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	3	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

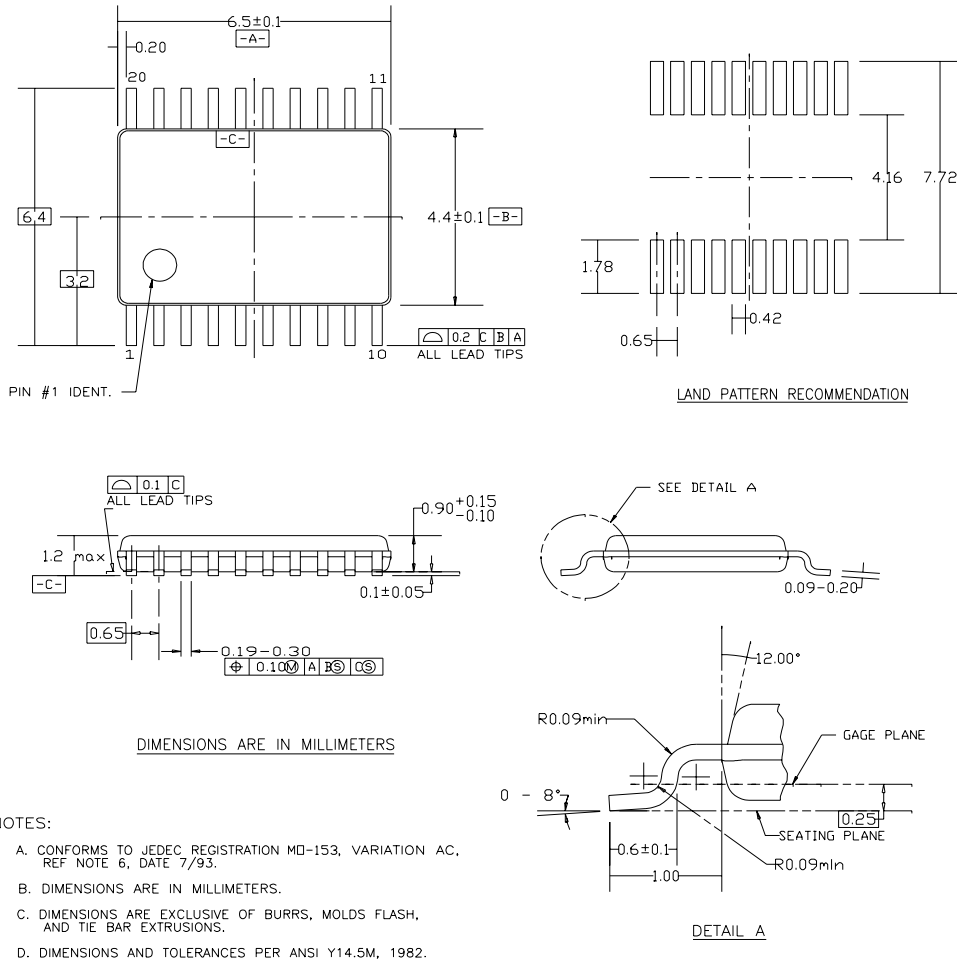


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

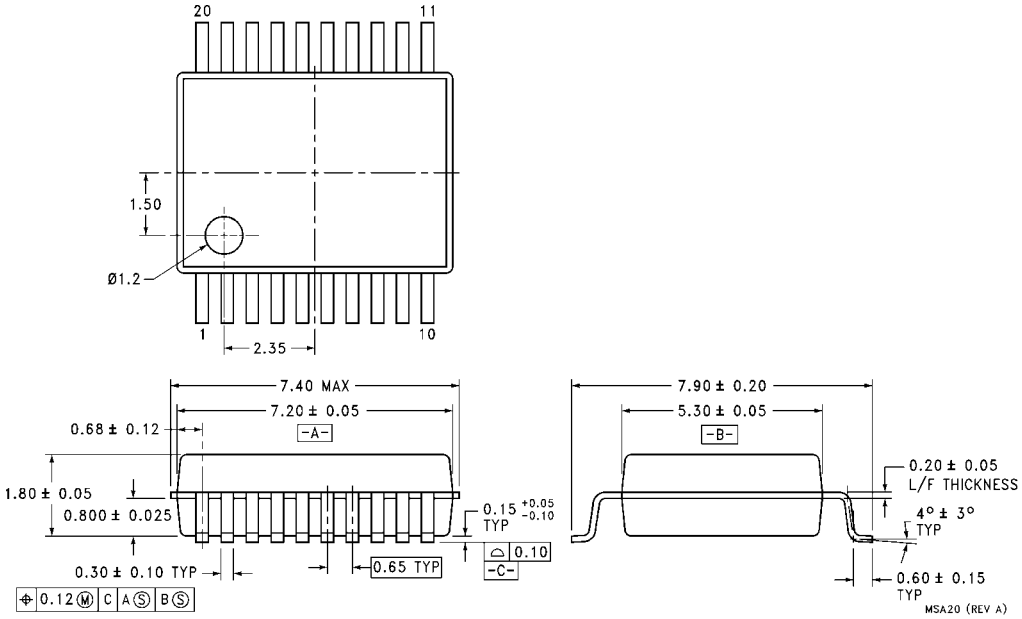
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

FAIRCHILD SEMICONDUCTOR™

July 1999
Revised August 1999

74LVT244 •74LVTH244
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVT244 and LVTH244 are octal buffers and line drivers designed to be employed as memory address drivers, clock drivers and bus oriented transmitters or receivers which provide improved PC board density.

The LVTH244 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal buffers and line drivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT244 and LVTH244 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

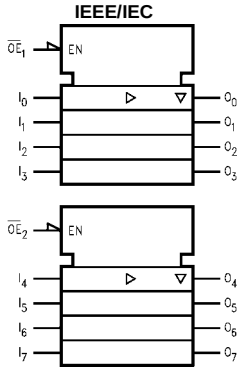
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH244), also available without bushold feature (74LVT244)
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 244
- Latch-up performance exceeds 500 mA

Ordering Code:

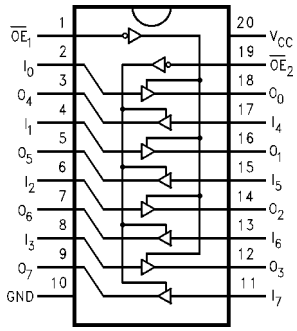
Order Number	Package Number	Package Description
74LVT244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVT244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVT244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVTH244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH244MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVTH244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Output

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC}–0.2			V	$I_{OH} = -100$ µA
			2.7	2.4			V	$I_{OH} = -8$ mA
			3.0	2.0			V	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	$I_{OL} = 100$ µA
			2.7			0.5	V	$I_{OL} = 24$ mA
			3.0			0.4	V	$I_{OL} = 16$ mA
			3.0			0.5	V	$I_{OL} = 32$ mA
			3.0			0.55	V	$I_{OL} = 64$ mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	$V_I = 0.8V$
				−75			µA	$V_I = 2.0V$
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500			µA	(Note 6)
I_I	Input Current		3.6			10	µA	$V_I = 5.5V$
		Control Pins	3.6			±1	µA	$V_I = 0V$ or V_{CC}
		Data Pins	3.6			−5	µA	$V_I = 0V$
						1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	$V_O = 0.5V$ to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	$V_O = 0.5V$
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	$V_O = 3.0V$
I_{OZH+}	3-STATE Output Leakage Current		3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled
I_{CCZ+}	Power Supply Current		3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)		3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH244).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.1		3.8	1.1	4.0	ns
t_{PHL}		1.3		3.9	1.3	4.2	
t_{PZH}	Output Enable Time	1.1		4.5	1.1	5.3	ns
t_{PZL}		1.4		4.4	1.4	5.0	
t_{PHZ}	Output Disable Time	1.9		4.9	1.9	5.1	ns
t_{PLZ}		1.8		4.4	1.8	4.4	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 11)						

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

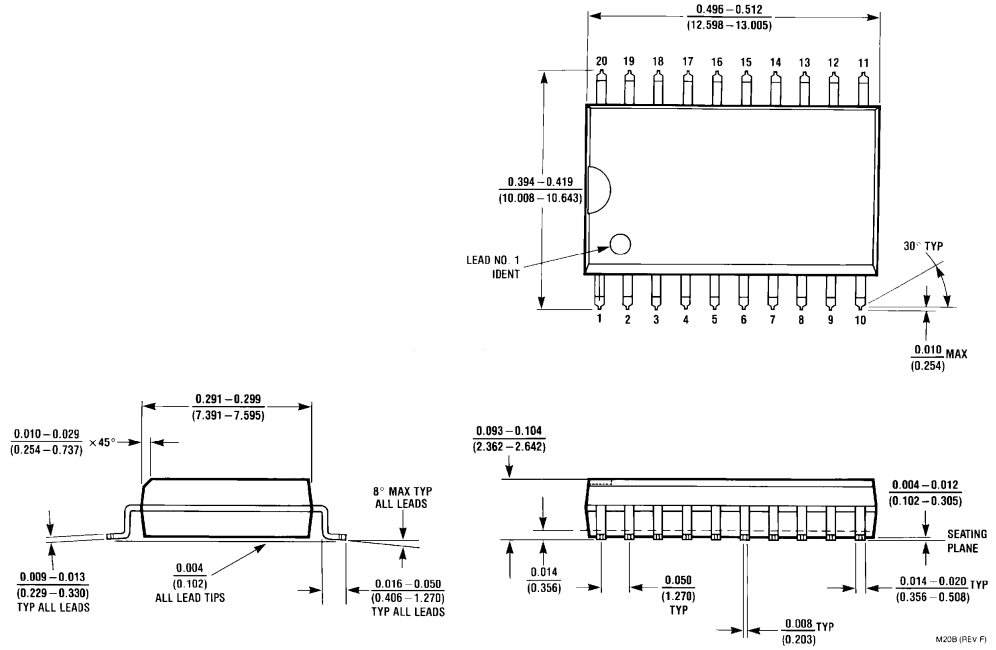
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance (Note 12)

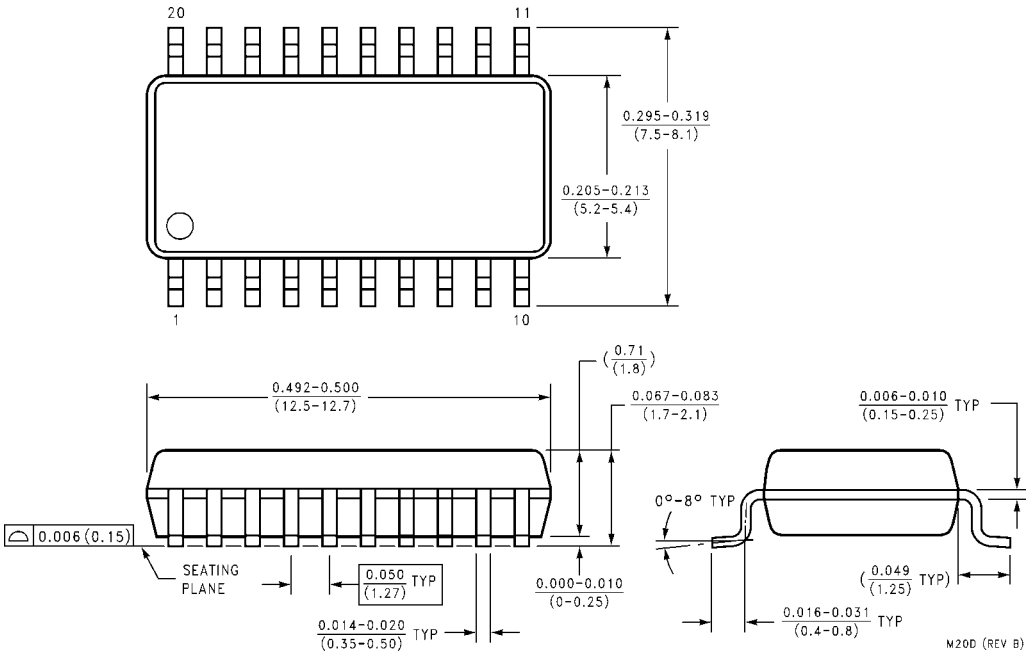
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	3	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

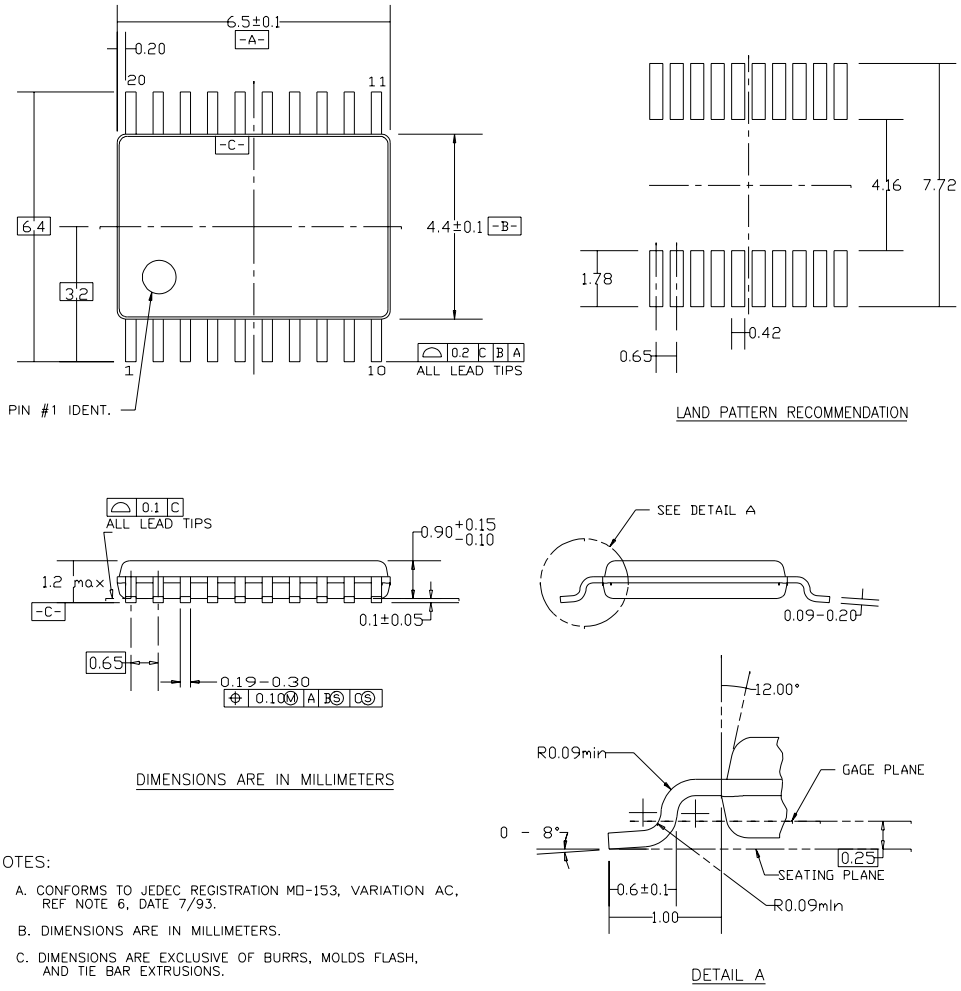


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

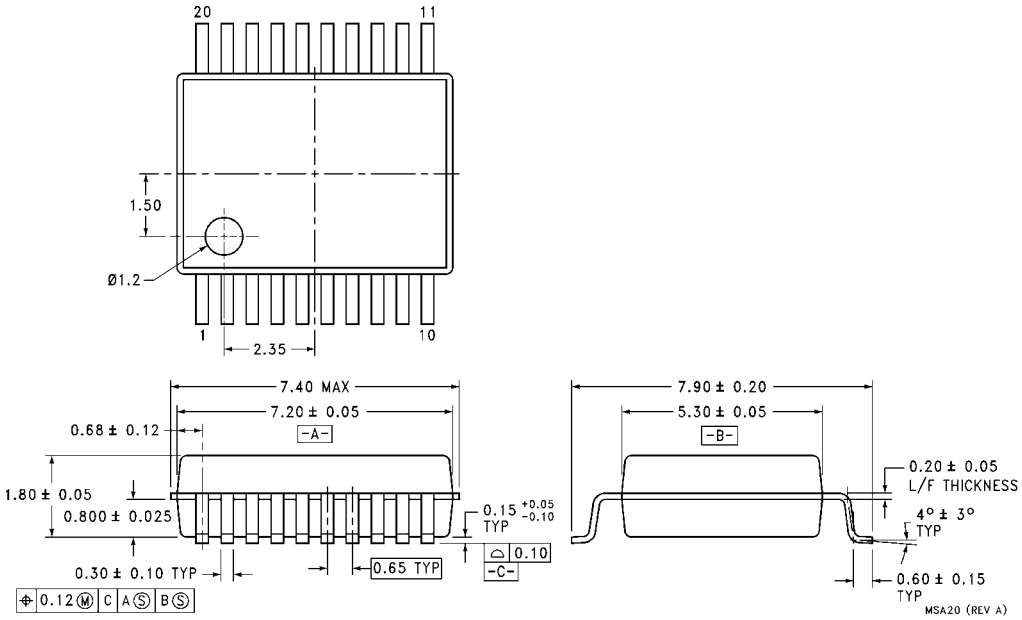
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

FAIRCHILD SEMICONDUCTOR™

November 1999
Revised January 2000

74LVT245 • 74LVTH245
Low Voltage Octal Bidirectional Transceiver with 3-STATE Inputs/Outputs

General Description

The LVT245 and LVTH245 contain eight non-inverting bidirectional buffers with 3-STATE outputs and are intended for bus-oriented applications. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

The LVTH245 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT245 and LVTH245 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

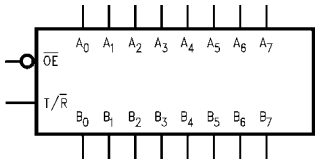
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH245), also available without bushold feature (74LVT245).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink, –32 mA/+64 mA
- Latch-up performance exceeds 500 mA

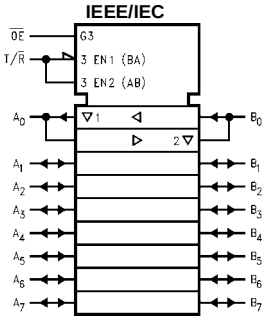
Ordering Code:

Order Number	Package Number	Package Description
74LVT245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVT245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVT245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVT245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVTH245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVTH245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

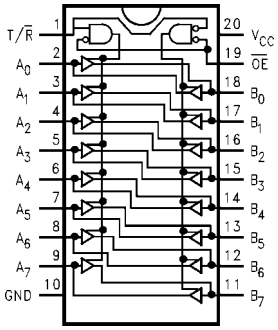
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	V_O > V_{CC} Output at HIGH State	mA
		128	V_O > V_{CC} Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C Min	T_A = −40°C to +85°C Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le$ 0.1V or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8		$V_O \ge V_{CC}$ − 0.1V
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} - 0.2		V	I_{OH} = −100 µA
			2.7	2.4		V	I_{OH} = − 8 mA
			3.0	2.0		V	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5	V	I_{OL} = 24 mA
			3.0		0.4	V	I_{OL} = 16 mA
			3.0		0.5	V	I_{OL} = 32 mA
			3.0		0.55	V	I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
(Note 3)				−75		µA	V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive		3.0	500		µA	(Note 4)
(Note 3)	Current to Change State			−500		µA	(Note 5)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6		−5	µA	V_I = 0V
					1	µA	V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0		±100	µA	0V ≤ V_I or $V_O \le$ 5.5V
$I_{PU/PD}$	Power Up/Down 3-STATE Current		0–1.5V		±100	µA	V_O = 0.5V to V_{CC} V_I = GND to V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.5V
I_{OZL} (Note 3)	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Max		
I_{OZH} (Note 3)	3-STATE Output Leakage Current	3.6		5	μA	$V_O = 3.6V$
$I_{OZH}+$	3-STATE Output Leakage Current	3.6		10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current	3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current	3.6		0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 6)	3.6		0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: Applies to Bushold versions only (LVTH245).

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay	1.2	3.6	1.2	4.0	ns
t_{PHL}		1.2	3.5	1.2	4.0	
t_{PZH}	Output Enable Time	1.3	5.5	1.3	7.1	ns
t_{PZL}		1.7	5.7	1.7	6.7	
t_{PHZ}	Output Disable	2.0	5.9	2.0	6.5	ns
t_{PLZ}		2.0	5.0	2.0	5.1	
t_{OSHL}	Output to Output Skew (Note 9)		1.0		1.0	ns
t_{OSLH}						

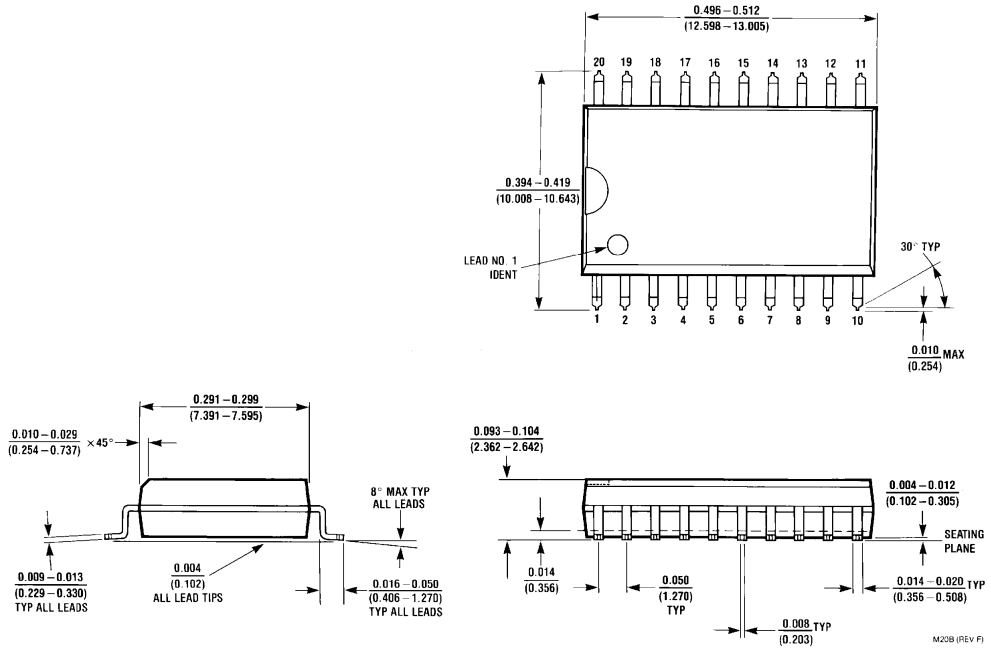
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 10)

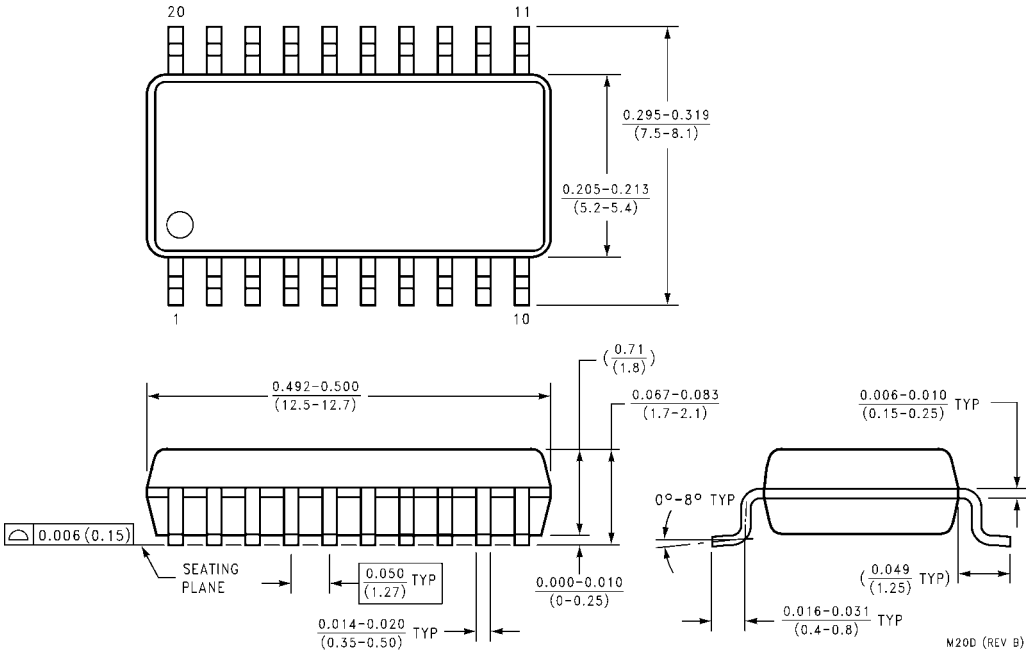
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

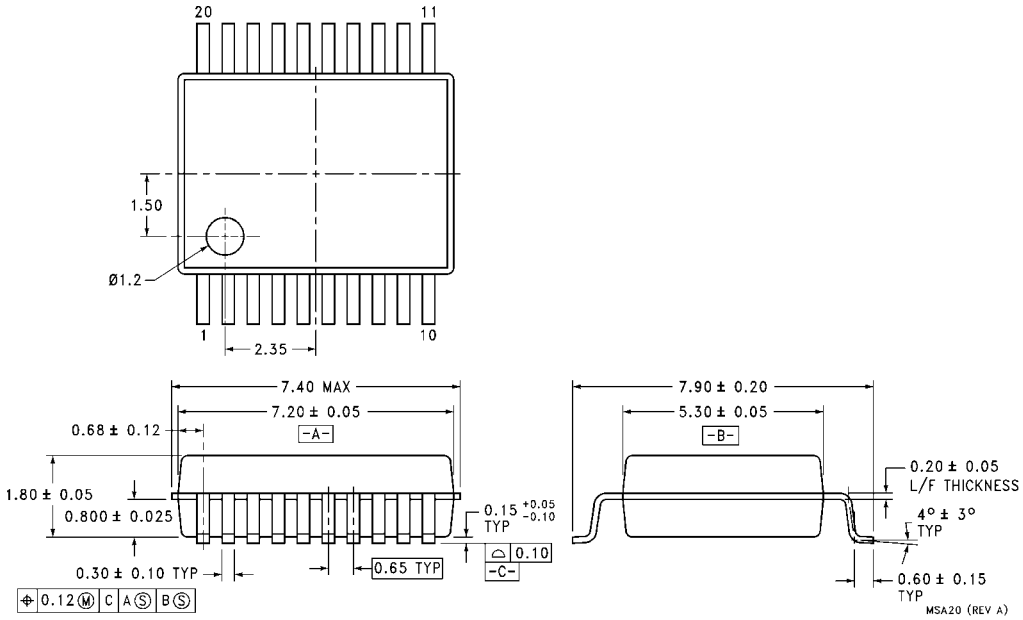


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



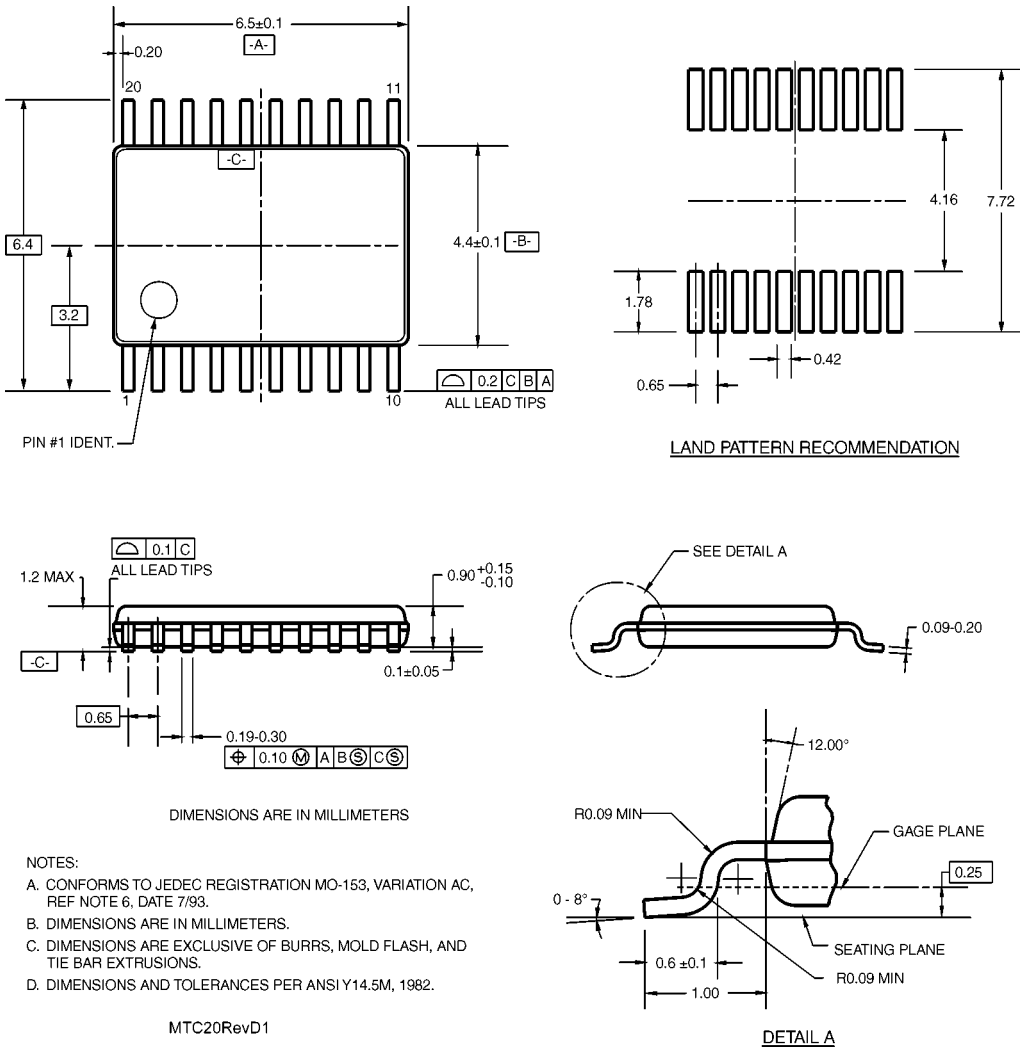
20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

FAIRCHILD SEMICONDUCTOR™

September 1999
Revised October 1999

74LVT373 • 74LVTH373
Low Voltage Octal Transparent Latch with 3-STATE Outputs

General Description

The LVT373 and LVTH373 consist of eight latches with 3-STATE outputs for bus organized system applications. The latches appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in a high impedance state.

The LVTH373 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal latches are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT373 and LVTH373 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

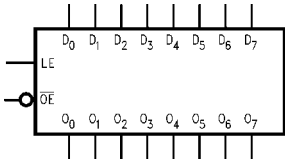
Features

- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH373), also available without bushold feature (74LVT373).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 373

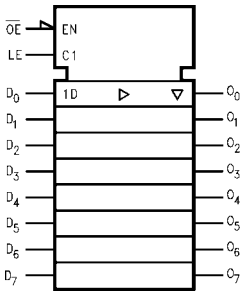
Ordering Code:

Order Number	Package Number	Package Description
74LVT373WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVT373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH373WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

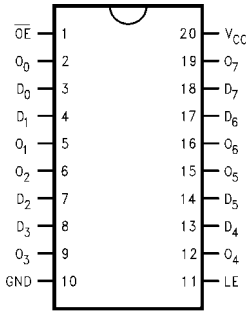
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Truth Table

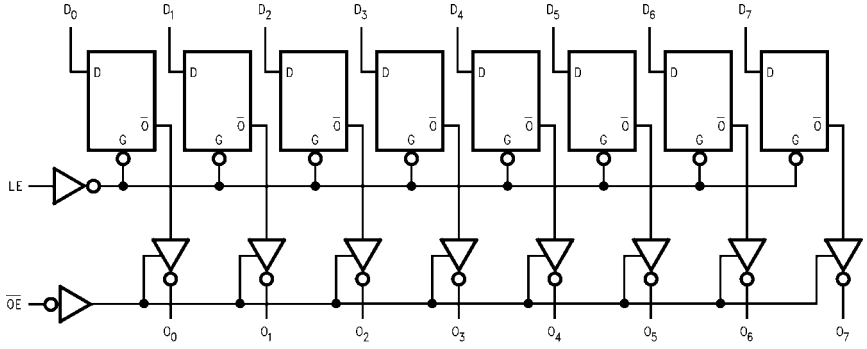
Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Functional Description

The LVT373 and LVTH373 contain eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage	2.7–3.6			0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage	2.7–3.6	$V_{CC} - 0.2$			V	$I_{OH} = -100$ µA
		2.7	2.4			V	$I_{OH} = -8$ mA
		3.0	2.0			V	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage	2.7			0.2	V	$I_{OL} = 100$ µA
		2.7			0.5	V	$I_{OL} = 24$ mA
		3.0			0.4	V	$I_{OL} = 16$ mA
		3.0			0.5	V	$I_{OL} = 32$ mA
		3.0			0.55	V	$I_{OL} = 64$ mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive	3.0	75			µA	$V_I = 0.8V$
			−75			µA	$V_I = 2.0V$
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State	3.0	500			µA	(Note 5)
			−500			µA	(Note 6)
I_I	Input Current	3.6			10	µA	$V_I = 5.5V$
	Control Pins	3.6			±1	µA	$V_I = 0V$ or V_{CC}
	Data Pins	3.6			−5	µA	$V_I = 0V$
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current	0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current	0–1.5V			±100	µA	$V_O = 0.5V$ to $3.0V$ V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current	3.6			−5	µA	$V_O = 0.5V$
I_{OZH}	3-STATE Output Leakage Current	3.6			5	µA	$V_O = 3.0V$
$I_{OZH}+$	3-STATE Output Leakage Current	3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to Bushold versions only (74LVTH373).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5		4.5	1.5	5.0	ns
t_{PLH}	D_n to O_n	1.5		4.5	1.5	4.9	
t_{PHL}	Propagation Delay	1.7		4.6	1.7	4.9	ns
t_{PLH}	LE to O_n	1.7		4.5	1.7	5.0	
t_{PZL}	Output Enable Time	1.3		4.8	1.3	5.9	ns
t_{PZH}		1.3		4.8	1.3	5.5	
t_{PLZ}	Output Disable Time	1.9		4.6	1.9	4.9	ns
t_{PHZ}		1.9		4.6	1.9	4.9	
t_W	LE Pulse Width	3.0			3.0		ns
t_S	Setup Time, D_n to LE	1.1			1.0		ns
t_H	Hold Time, D_n to LE	1.4			1.4		ns

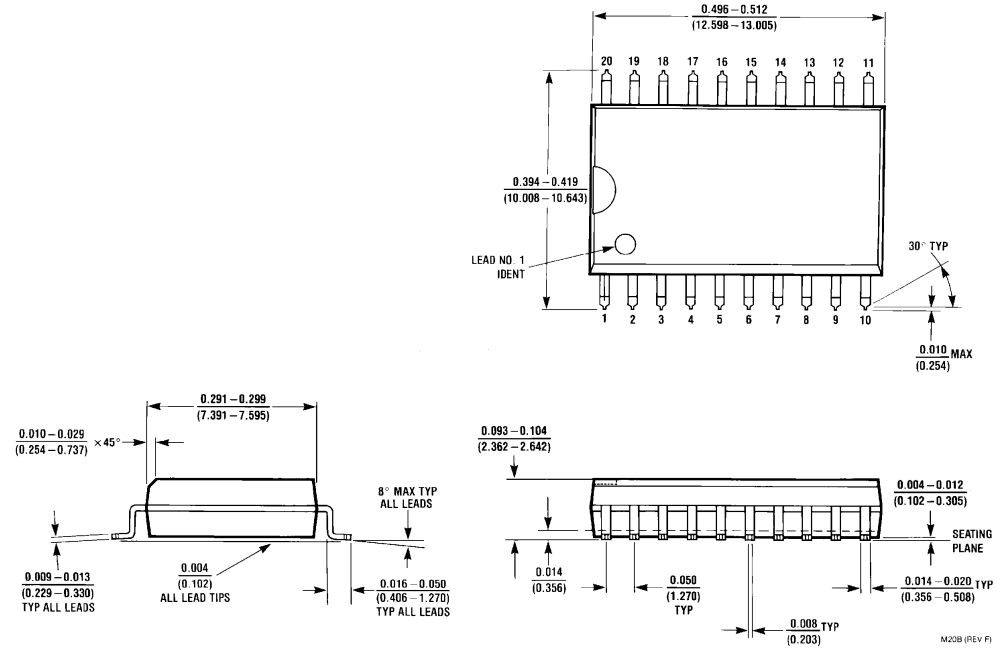
Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Capacitance (Note 11)

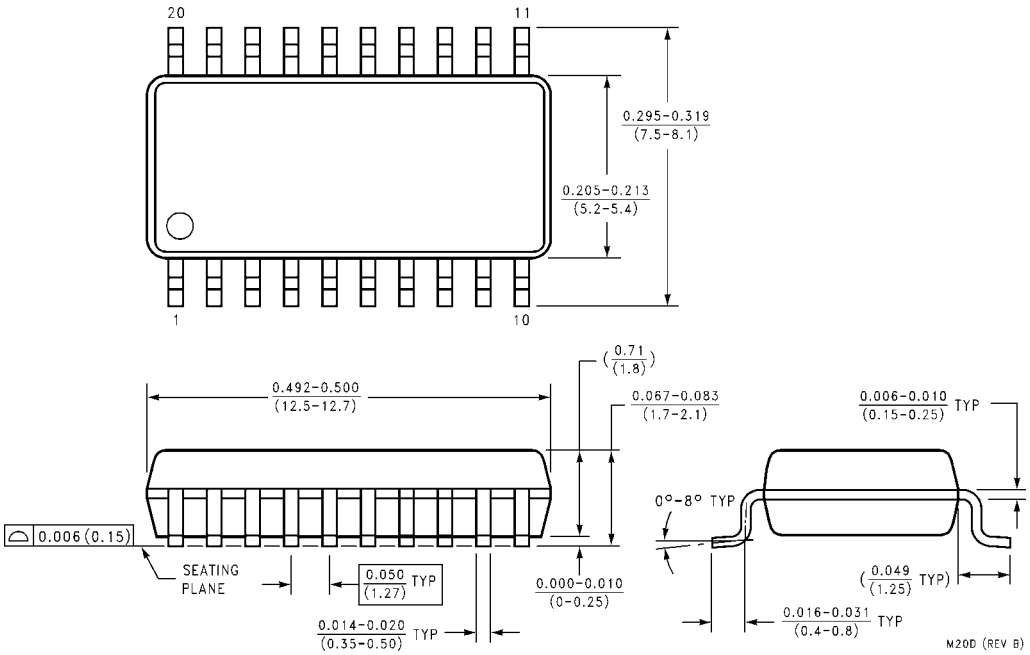
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = OPEN, V_I = 0V or V_{CC}	3	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, V_O= 0V or V_{CC}	5	pF

Note 11: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

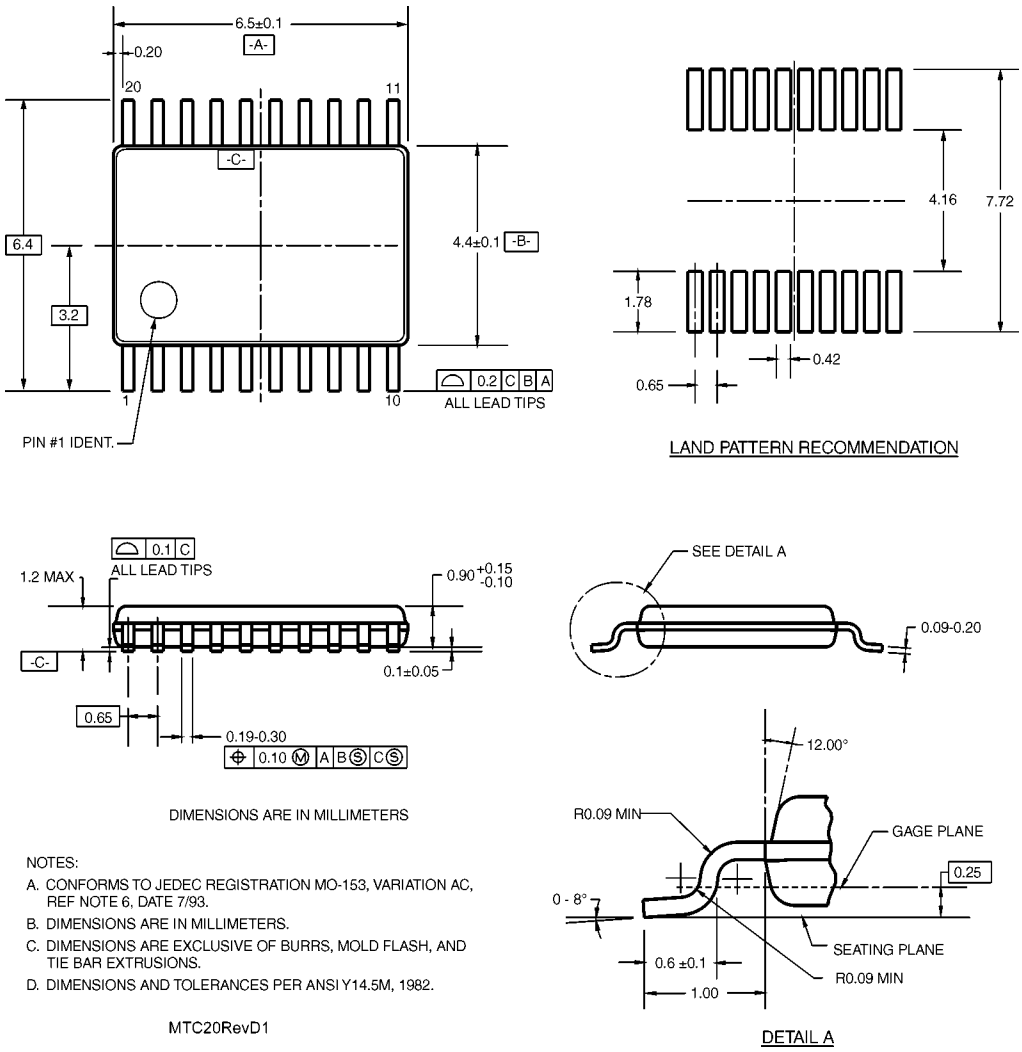


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

September 1999
Revised October 1999

74LVT374 • 74LVTH374
Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVT374 and LVTH374 are high-speed, low-power octal D-type flip-flops featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

The LVTH374 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal flip-flops are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT374 and LVTH374 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

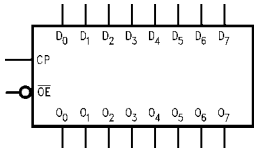
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH374), also available without bushold feature (74LVT374).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 374
- Latch-up performance exceeds 500 mA

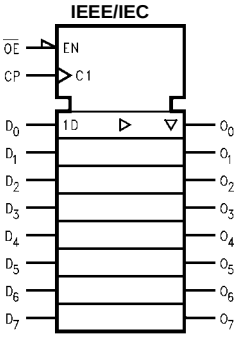
Ordering Code:

Order Number	Package Number	Package Description
74LVT374WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVT374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH374WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

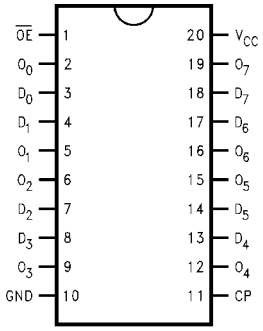
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

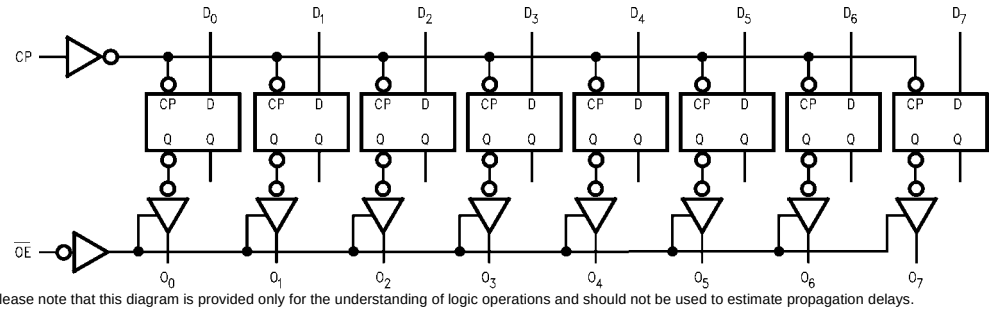
Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	L	L	O_o
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
O_o = Previous O_o before HIGH-to-LOW of CP

Functional Description

The LVT374 and LVTH374 consist of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}(V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage	2.7–3.6			0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage	2.7–3.6	$V_{CC} - 0.2$			V	$I_{OH} = -100$ µA
		2.7	2.4			V	$I_{OH} = -8$ mA
		3.0	2.0			V	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage	2.7			0.2	V	$I_{OL} = 100$ µA
		2.7			0.5	V	$I_{OL} = 24$ mA
		3.0			0.4	V	$I_{OL} = 16$ mA
		3.0			0.5	V	$I_{OL} = 32$ mA
		3.0			0.55	V	$I_{OL} = 64$ mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive	3.0	75			µA	$V_I = 0.8V$
			−75			µA	$V_I = 2.0V$
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State	3.0	500			µA	(Note 5)
			–500			µA	(Note 6)
I_I	Input Current	3.6			10	µA	$V_I = 5.5V$
	Control Pins	3.6			±1	µA	$V_I = 0V$ or V_{CC}
	Data Pins	3.6			−5	µA	$V_I = 0V$
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current	0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current	0–1.5V			±100	µA	$V_O = 0.5V$ to $3.0V$ V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current	3.6			−5	µA	$V_O = 0.5V$
I_{OZH}	3-STATE Output Leakage Current	3.6			5	µA	$V_O = 3.0V$
I_{OZH+}	3-STATE Output Leakage Current	3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ+}	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to Bushold versions only (74LVTH374).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	160			160		MHz
t_{PHL}	Propagation Delay	1.8		4.9	1.8	5.1	ns
t_{PLH}	CP to O_n	1.8		4.8	1.8	5.2	
t_{PZL}	Output Enable Time	1.3		5.0	1.3	5.8	ns
t_{PZH}		1.6		4.7	1.6	5.3	
t_{PLZ}	Output Disable Time	1.9		4.6	1.9	4.9	ns
t_{PHZ}		2.0		4.7	2.0	5.0	
t_W	Pulse Width	3.0			3.0		ns
t_S	Setup Time	1.5			2.0		ns
t_H	Hold Time	0.8			0.0		ns

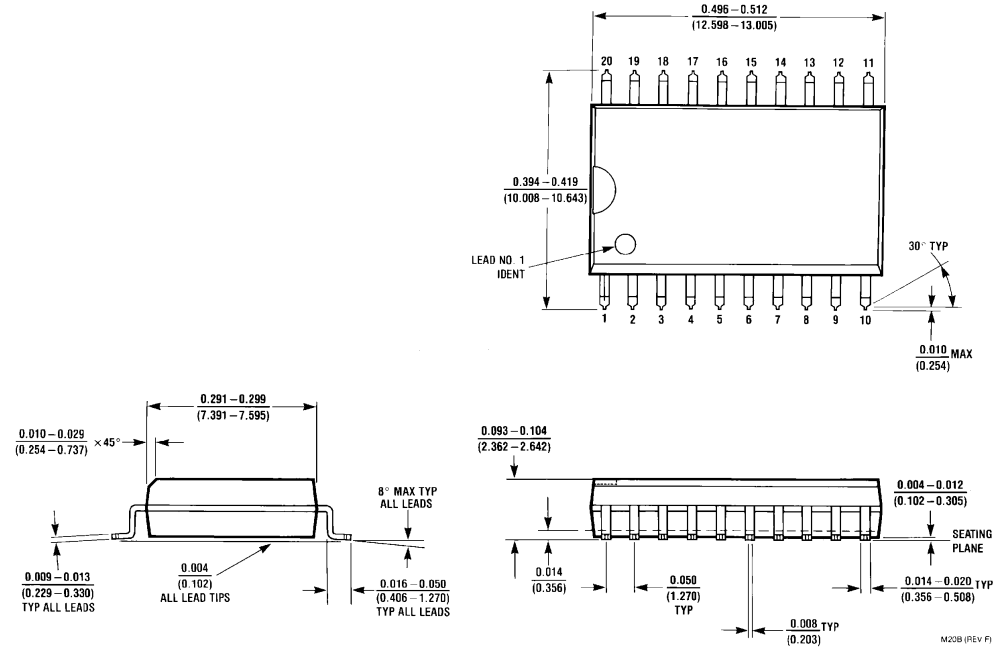
Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Capacitance (Note 11)

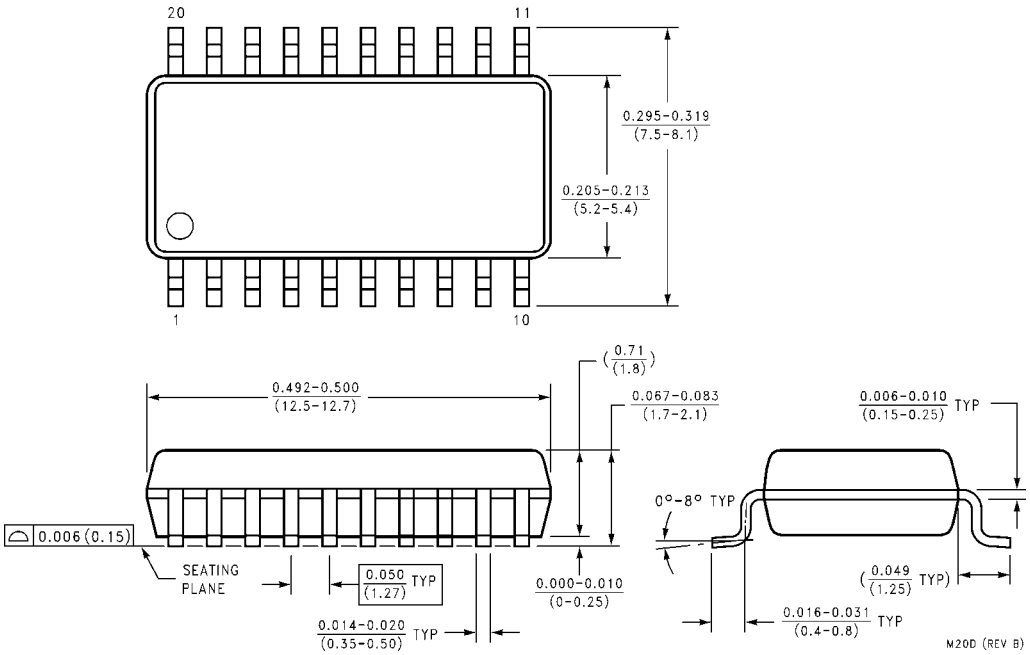
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	3	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	5	pF

Note 11: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

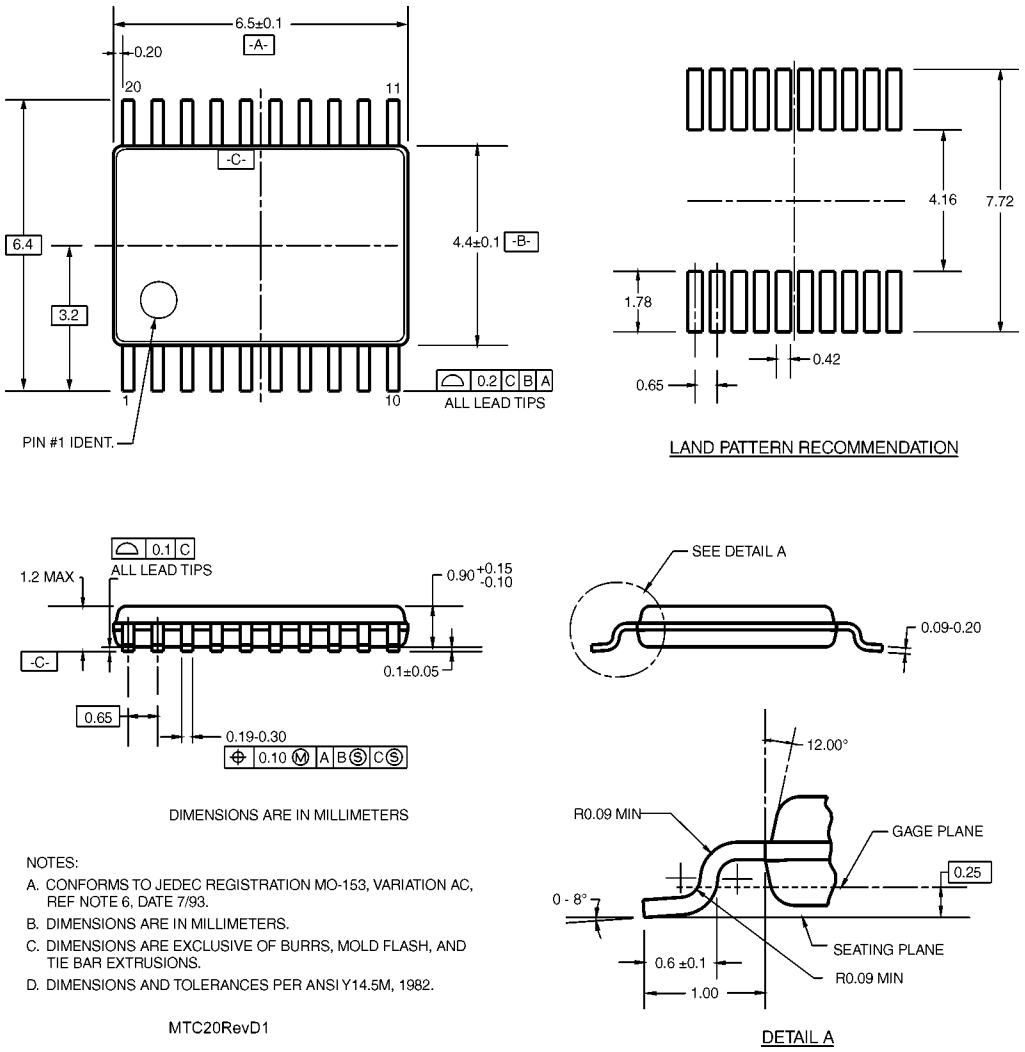


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20RevD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

ADVANCE INFORMATION
February 1996

74LVT543
3.3V ABT Octal Registered Transceiver with TRI-STATE® Outputs

General Description

The 'LVT543 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow.

These octal registered transceivers is/are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT543 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

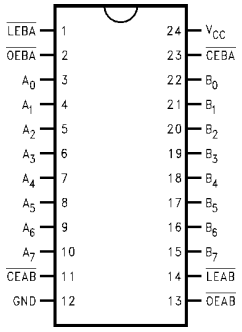
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SOIC JEDEC and TSSOP
- Functionally compatible with the 74 series 543
- Latch-up performance exceeds 500 mA

Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs
$\overline{LEAB}$, $\overline{LEBA}$	Latch Enable Inputs
$\overline{CEAB}$, $\overline{CEBA}$	Chip Enable Inputs
A_0–A_7	Side A Inputs or TRI-STATE Outputs
B_0–B_7	Side B Inputs or TRI-STATE Outputs

Connection Diagram

Pin Assignment for SOIC, SSOP II and TSSOP



TL/F/12448–1

	SOIC JEDEC	TSSOP	SSOP II
Order Number	74LVT543WM 74LVT543WMX	74LVT543MTC 74LVT543MTCX	74LTV543MSA 74LTV543MSAX
See NS Package Number	M24B	MTC24	MSA24

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Functional Description

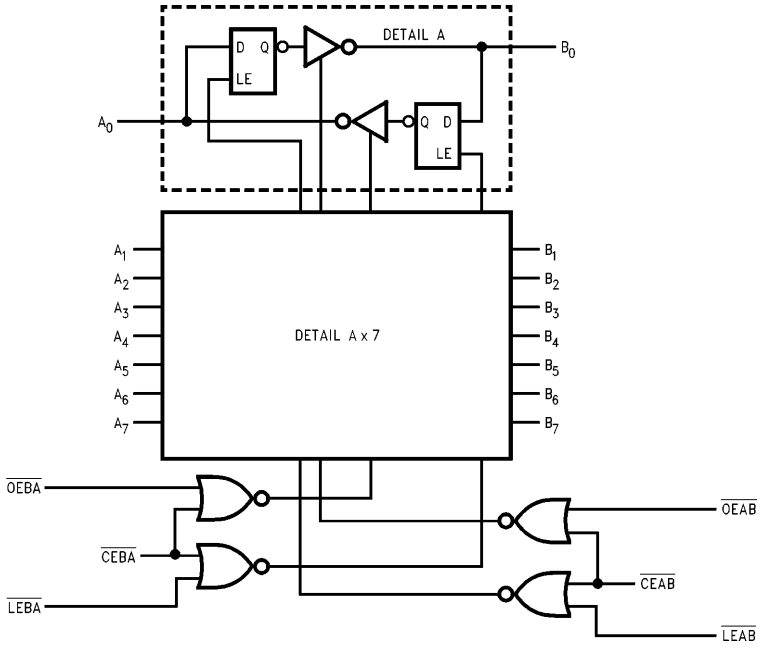
The 'LVT543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable ($\overline{CEAB}$) input must be low in order to enter data from the A port or take data from the B port as indicated in the Data I/O Control Table. With $\overline{CEAB}$ low, a low signal on ($\overline{LEAB}$) input makes the A to B latches transparent; a subsequent low to high transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both low, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$.

Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = High Voltage Level
L = Low Voltage Level
X = Immaterial

Logic Diagram



TL/F/12448–2

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1999
Revised March 1999

74LVT573 • 74LVTH573
Low Voltage Octal Transparent Latch with 3-STATE Outputs

General Description

The LVT573 and LVTH573 consist of eight latches with 3-STATE outputs for bus organized system applications. The latches appear transparent to the data when Latch Enable (LE) is HIGH. When LE is low, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state.

The LVTH573 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal latches are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT573 and LVTH573 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

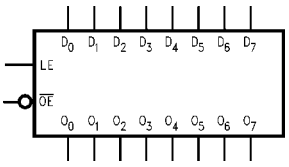
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH573), also available without bushold feature (74LVT573).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Functionally compatible with the 74 series 573
- Latch-up performance exceeds 500 mA

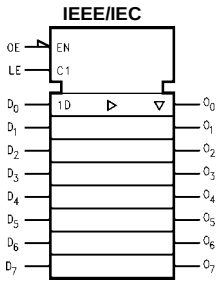
Ordering Code:

Order Number	Package Number	Package Description
74LVT573WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVT573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVT573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVT573MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVTH573WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVTH573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH573MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide

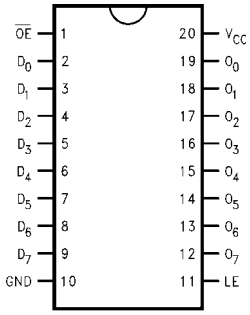
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level

L = LOW Voltage Level

Z = High Impedance

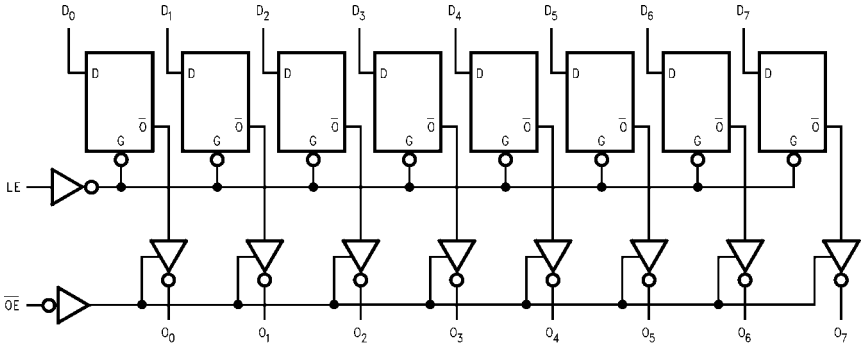
X = Immaterial

O_0 = Previous O_0 before HIGH to LOW transition of Latch Enable

Functional Description

The LVT573 and LVTH573 contain eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW, the latches store the information that was present on the D-type inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at High State	mA
		128	$V_O > V_{CC}$ Output at Low State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C Min	Typ (Note 3)	Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			2.7	2.4				I_{OH} = −8 mA
			3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5		I_{OL} = 24 mA
			3.0			0.4		I_{OL} = 16 mA
			3.0			0.5		I_{OL} = 32 mA
			3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive		3.0	500			µA	(Note 5)
	Current to Change State			−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0			±100	µA	0V ≤ V_I or V_O ≤ 5.5V
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V, V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}	3-STATE Output Leakage Current	3.6			5	μA	$V_O = 3.0V$
$I_{OZH}+$	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH573).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5		4.4	1.5	4.9	ns
t_{PLH}	D_n to O_n	1.5		4.1	1.5	4.7	
t_{PHL}	Propagation Delay	1.9		4.4	1.9	4.9	ns
t_{PLH}	LE to O_n	1.9		4.4	1.9	5.0	
t_{PZL}	Output Enable Time	1.5		5.1	1.5	6.6	ns
t_{PZH}		1.5		5.1	1.5	5.9	
t_{PLZ}	Output Disable Time	2.0		4.6	2.0	4.9	ns
t_{PHZ}		2.0		4.9	2.0	5.5	
t_S	Setup Time, D_n to LE	0.7			0.6		ns
t_H	Hold Time, D_n to LE	1.5			1.7		ns
t_W	LE Pulse Width	3.0			3.0		ns
t_{OSHL}	Output to Output Skew (Note 11)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

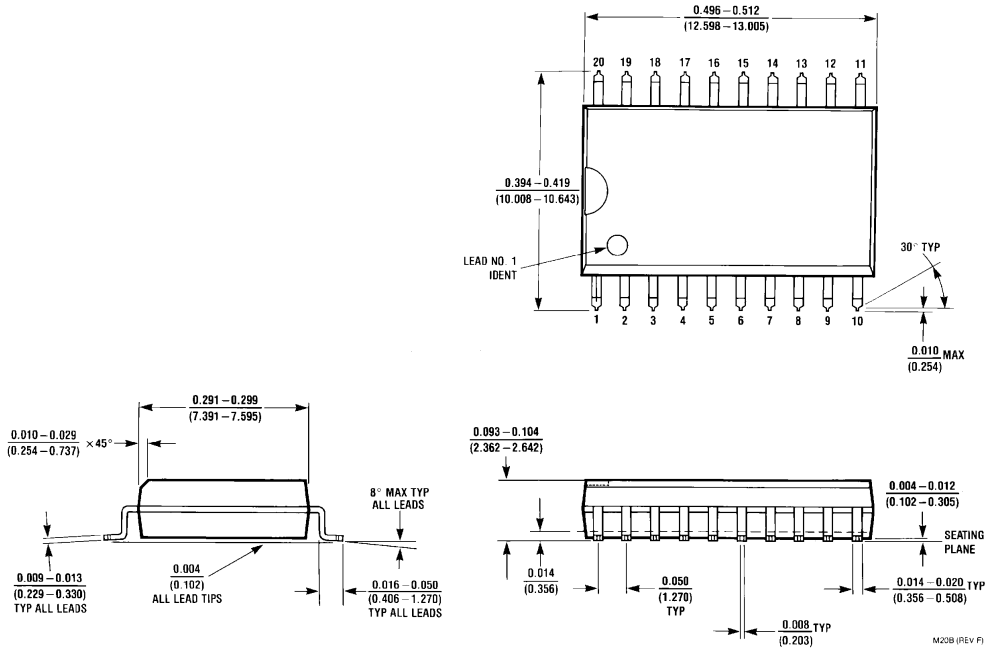
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 12)

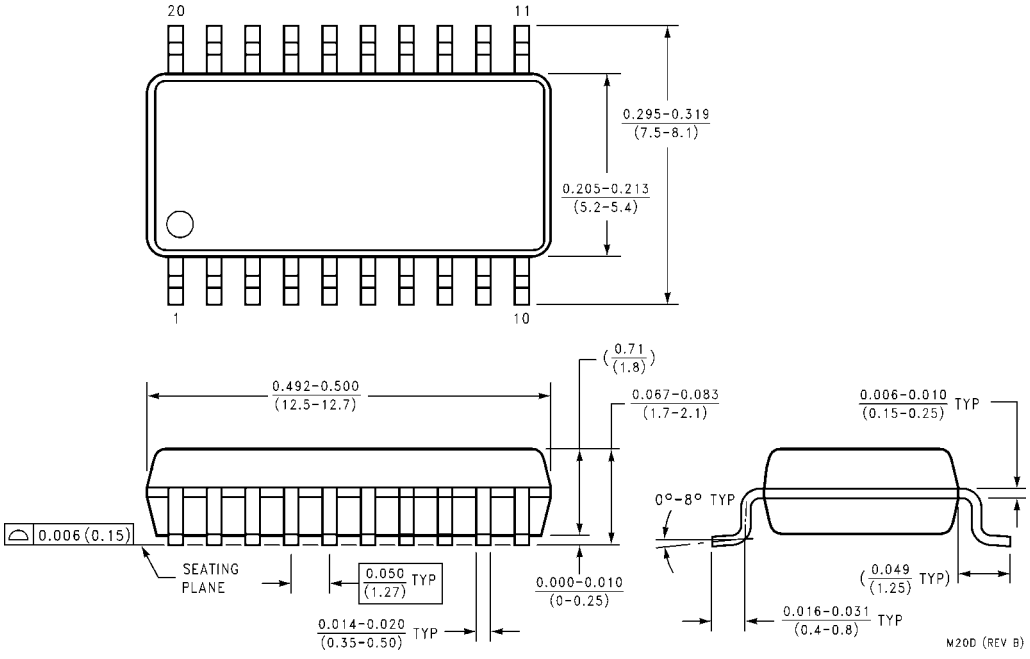
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

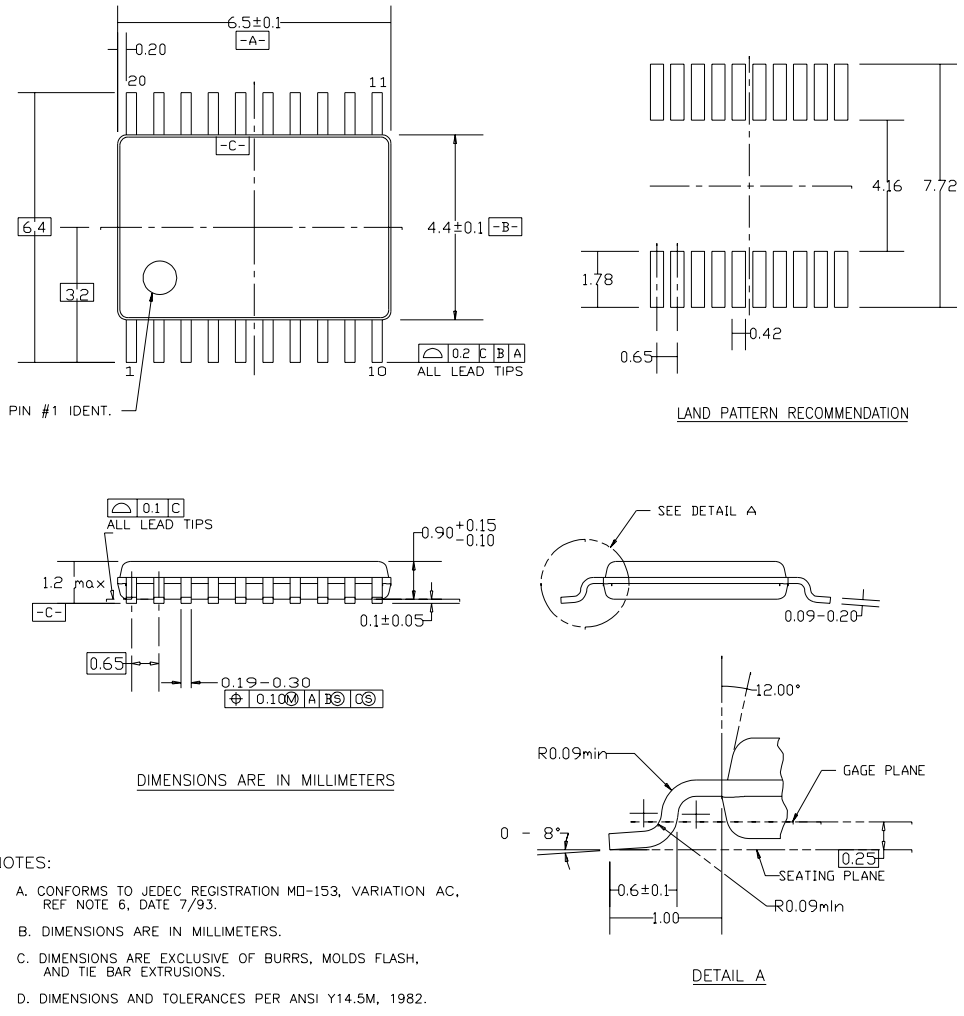


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, .300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

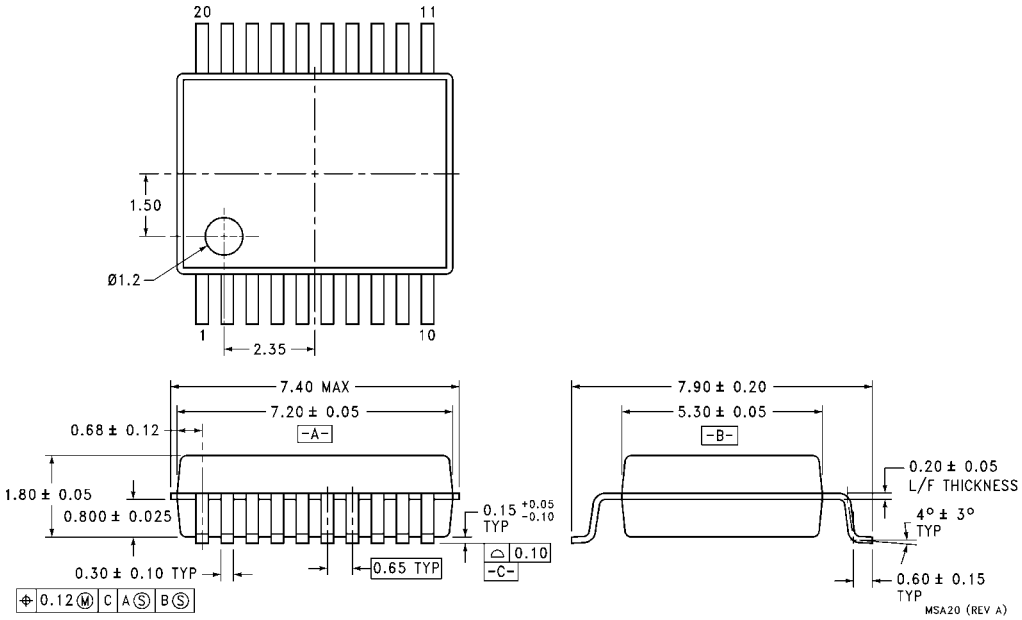
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1999
Revised March 1999

74LVT574 • 74LVTH574
Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVT574 and LVTH574 are high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops.

The LVTH574 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal flip-flops are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT574 and LVTH574 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

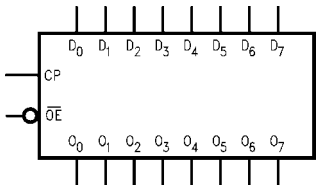
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH574), also available without bushold feature (74LVT574).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 574
- Latch-up performance exceeds 500 mA

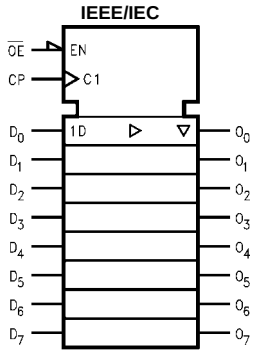
Ordering Code:

Order Number	Package Number	Package Description
74LVT574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, .300" Wide
74LVT574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVT574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVT574MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LVTH574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, .300" Wide
74LVTH574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVTH574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH574MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide

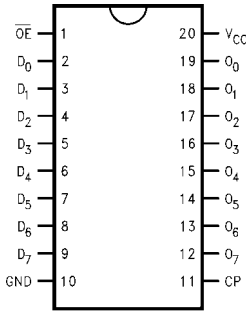
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

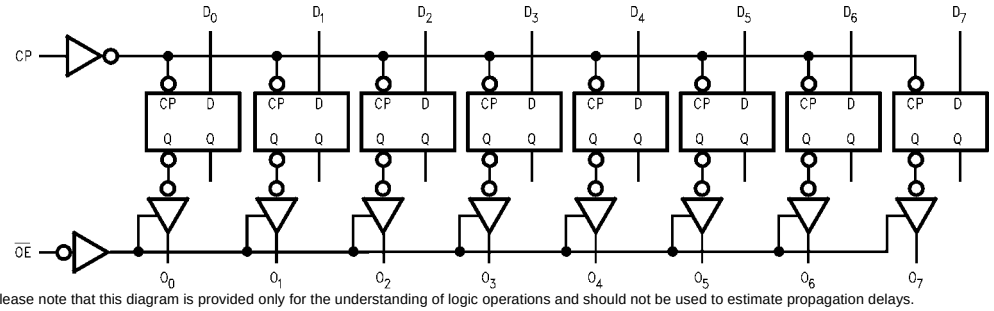
Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	L	L	O_o
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition
O_o = Previous O_o before HIGH to LOW of CP

Functional Description

The LVT574 and LVTH574 consist of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in High or Low State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at High State	mA
		128	$V_O > V_{CC}$ Output at Low State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	High-Level Output Current		−32	mA
I_{OL}	Low-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
			2.7	2.4				I_{OH} = −8 mA
			3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	I_{OL} = 100 µA
			2.7			0.5		I_{OL} = 24 mA
			3.0			0.4		I_{OL} = 16 mA
			3.0			0.5		I_{OL} = 32 mA
			3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$ (Note 4)	Bushold Input Minimum Drive		3.0	75			µA	V_I = 0.8V
				−75				V_I = 2.0V
$I_{I(OD)}$ (Note 4)	Bushold Input Over-Drive Current to Change State		3.0	500			µA	(Note 5)
				−500				(Note 6)
I_I	Input Current		3.6			10	µA	V_I = 5.5V
		Control Pins	3.6			±1		V_I = 0V or V_{CC}
		Data Pins	3.6			−5		V_I = 0V
						1		V_I = V_{CC}
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	V_O = 0.5V
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	V_O = 3.0V

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 3)	Max		
I_{OZH}+	3-STATE Output Leakage Current	3.6			10	μA	$V_{CC} < V_O \leq 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs High
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs Low
I_{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current	3.6			0.19	mA	$V_{CC} \leq V_O \leq 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: Applies to bushold versions only (74LVTH574).

Note 5: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 7: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 9)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 9)

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 10)	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150			150		MHz
t_{PHL}	Propagation Delay	1.8		4.6	1.8	5.3	ns
t_{PLH}	CP to O_n	1.8		4.5	1.8	5.3	
t_{PZL}	Output Enable Time	1.5		5.2	1.5	6.1	ns
t_{PZH}		1.5		4.8	1.5	5.9	
t_{PLZ}	Output Disable Time	2.0		4.4	2.0	4.4	ns
t_{PHZ}		2.0		4.8	2.0	5.1	
t_S	Setup Time	2.0			2.4		ns
t_H	Hold Time	0.3			0.0		ns
t_W	Pulse Width	3.3			3.3		ns
t_{OSHL}	Output to Output Skew (Note 11)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

Note 10: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

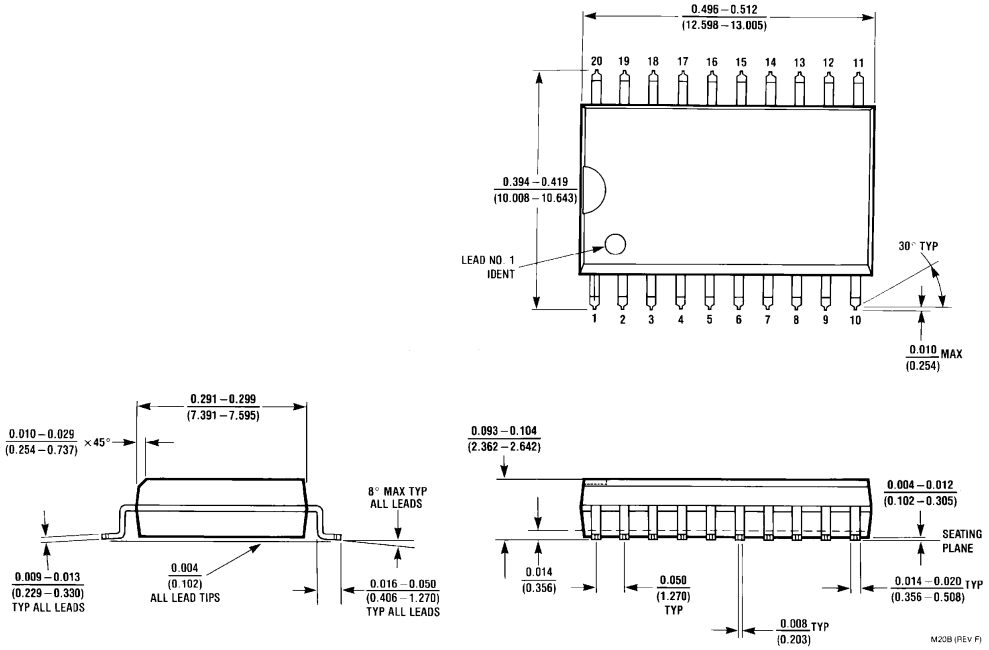
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 12)

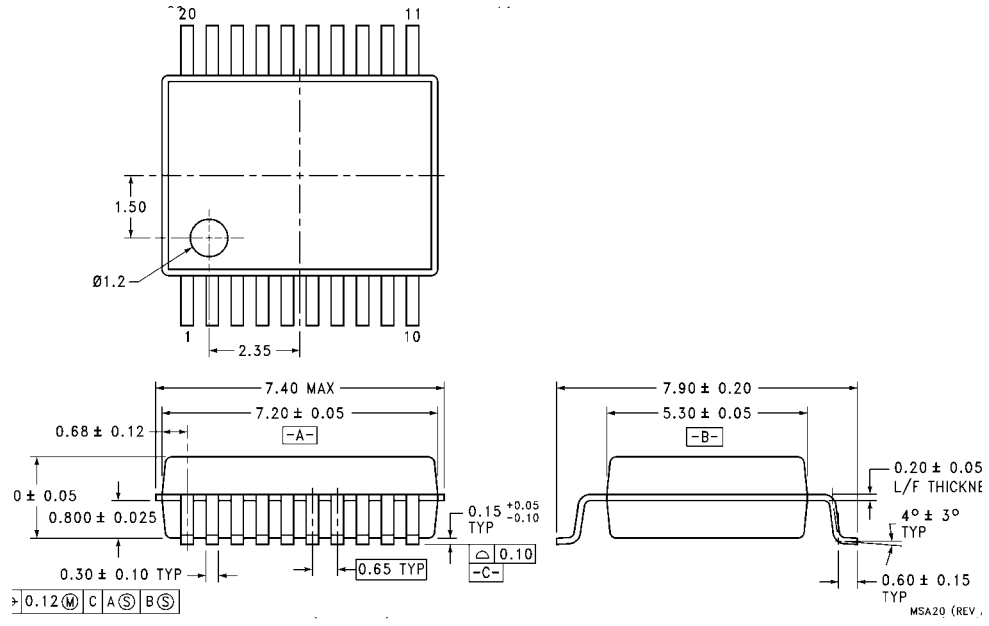
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

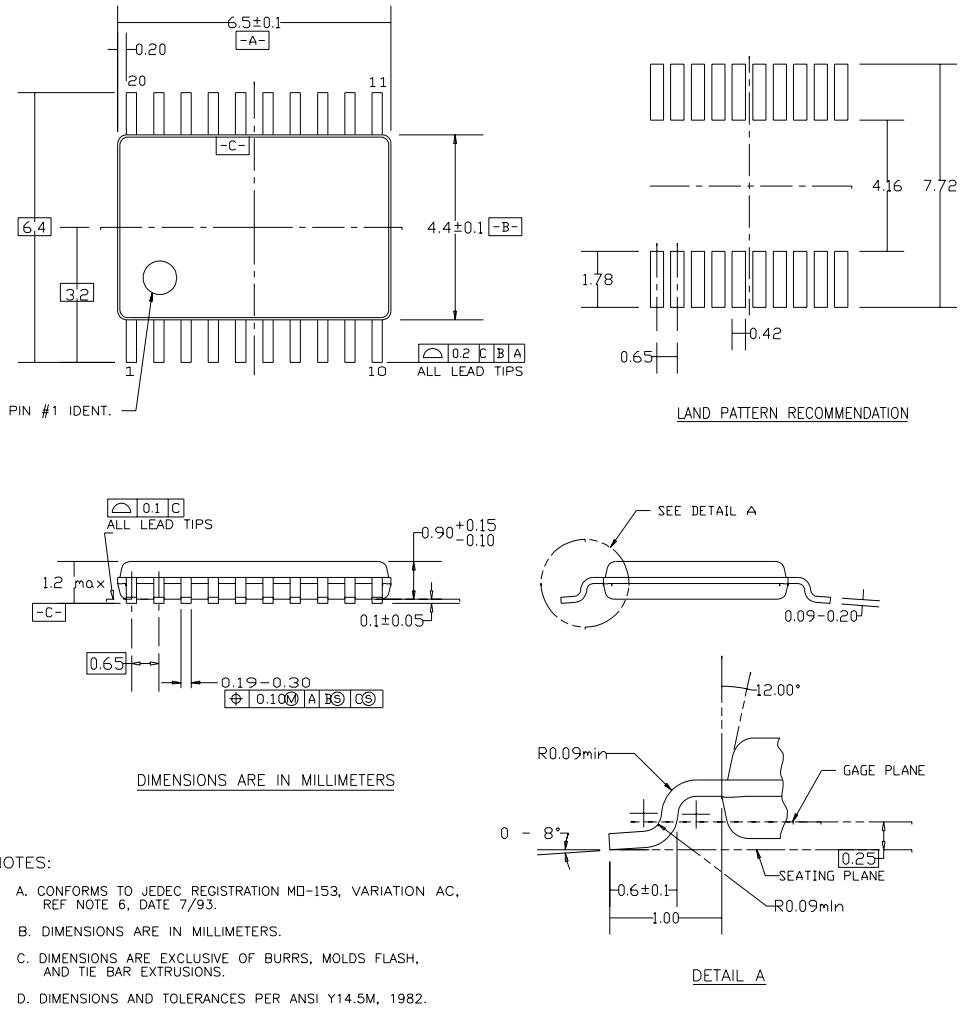


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, .300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

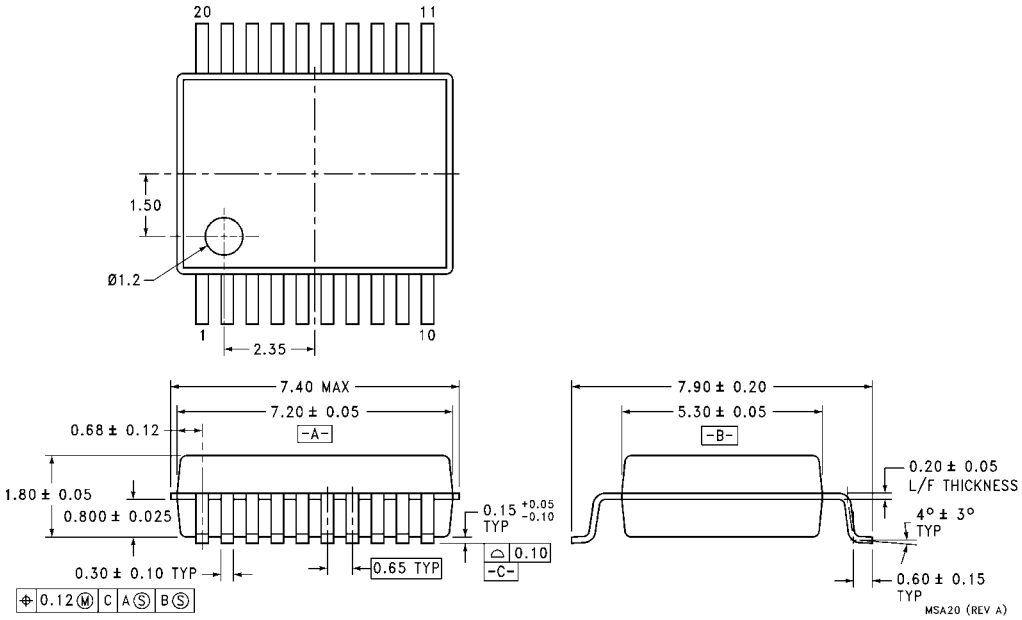
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
Package Number MSA20

National Semiconductor

ADVANCE INFORMATION
October 1995

74LVT646
3.3V ABT Octal Transceiver/Register with TRI-STATE® Outputs

General Description

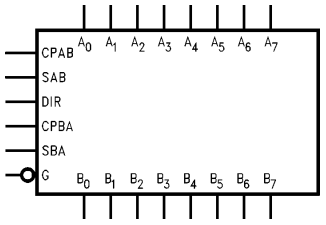
The LVT646 consist of registered bus transceiver circuits, with outputs, D-type flip-flops, and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate clock pin (CPAB or CPBA). The four fundamental handling functions available are illustrated in *Figures 1–4*.

The bus transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT646 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused input
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SOIC JEDEC, and TSSOP
- Functionally compatible with the 74 series 646
- Latch-up performance exceeds 500 mA

Logic Symbols



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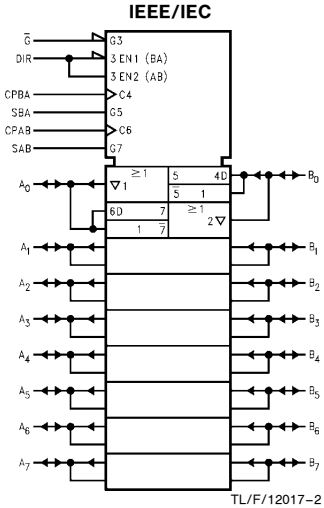
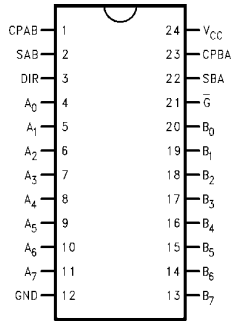
IEEE/IEC



TL/F/12017–2

Connection Diagram

Pin Assignment for SOIC and TSSOP



TL/F/12017–3

Pin Names	Description
A_0–A_7	Data Register A Inputs Data Register A Outputs
B_0–B_7	Data Register B Inputs Data Register B Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
$\overline{G}$	Output Enable Input
DIR	Direction Control Input

	SOIC JEDEC	TSSOP JEDEC
Order Number	74LVT646WM 74LVT646WMX	74LVT646MTCX
See NS Package Number	M24B	MTC24

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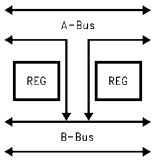
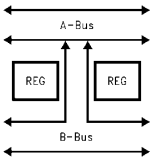
Real Time Transfer A-Bus to B-Bus



TL/F/12017–4

FIGURE 1

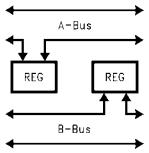
Real Time Transfer B-Bus to A-Bus



TL/F/12017–5

FIGURE 2

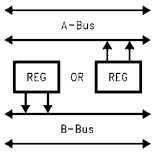
Storage from Bus to Register



TL/F/12017–6

FIGURE 3

Transfer from Register to Bus



TL/F/12017–7

FIGURE 4

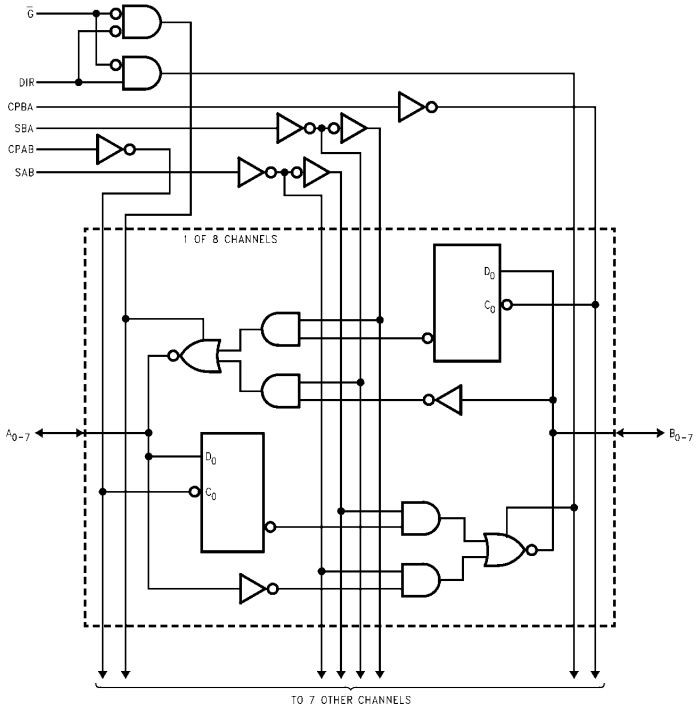
Truth Table (Note)

Inputs						Data I/O		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X	Input	Input	Isolation
H	X	↑	X	X	X			Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X	Input	Output	A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X			Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L	Output	Input	B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L			Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

Note: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial ↑ = LOW-to-HIGH Transition

Logic Diagram



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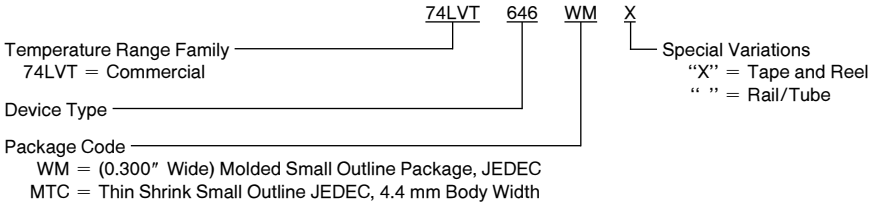
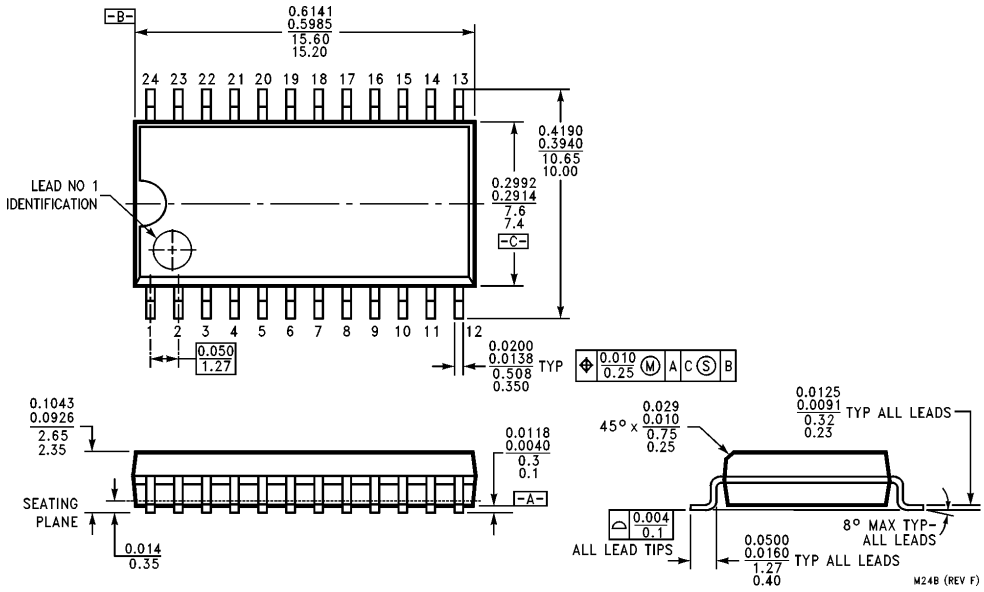
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

74LVT646 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

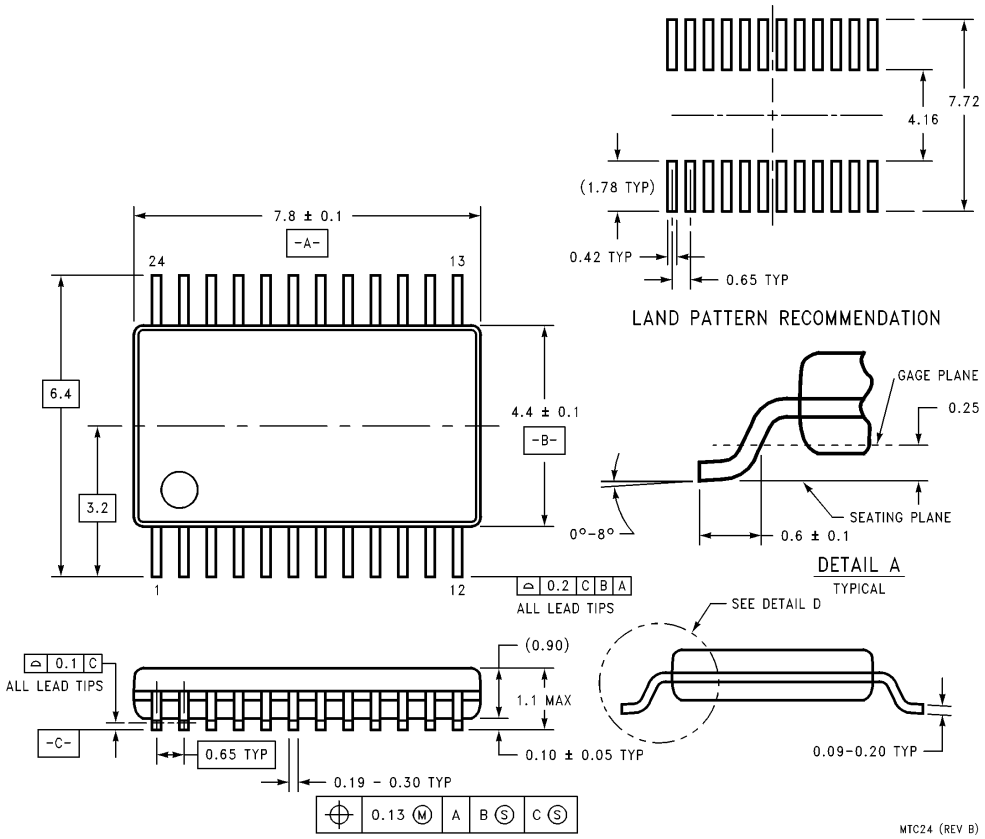


Physical Dimensions $\frac{\text{inches}}{(\text{millimeters})}$



24-Lead (0.300″ Wide) Molded Small Outline Package, JEDEC
Order Number 74LVT646WM or 74LVT646WMX
NS Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Molded Thin Shrink Small Outline Package, JEDEC
Order Number 74LVT646MTCX
NS Package Number MTC24

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

ADVANCE INFORMATION
October 1995

74LVT652
3.3V ABT Octal Transceiver/Register with TRI-STATE® Outputs

General Description

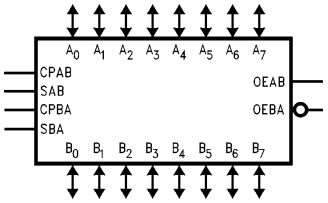
The LVT652 consists of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function.

These bus/octal buffers and line drivers is/are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT652 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

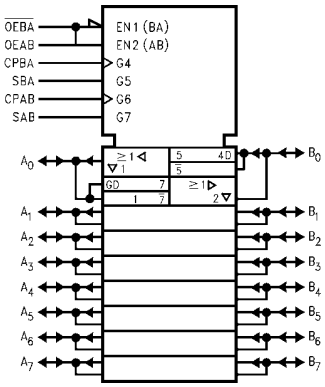
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink −32 mA/+64 mA
- Available in SOIC JEDEC and TSSOP
- Functionally compatible with the 74 series 652
- Latch-up performance exceeds 500 mA

Logic Symbols



TL/F/12018–8

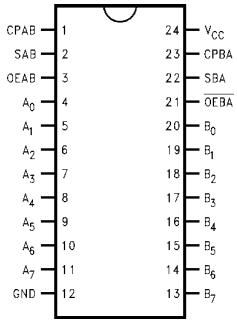
IEEE/IEC



TL/F/12018–7

Connection Diagram

Pin Assignment for SOIC and TSSOP



TL/F/12018–1

Pin Names	Description
A_0–A_7	Data Register A Inputs/ TRI-STATE Outputs
B_0–B_7	Data Register B Inputs/ TRI-STATE Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{OEBA}$	Output Enable Inputs

	SOIC JEDEC	TSSOP JEDEC
Order Number	74LVT652WM 74LVT652WMX	74LVT652MTCX
See NS Package Number	M24B	MTC24

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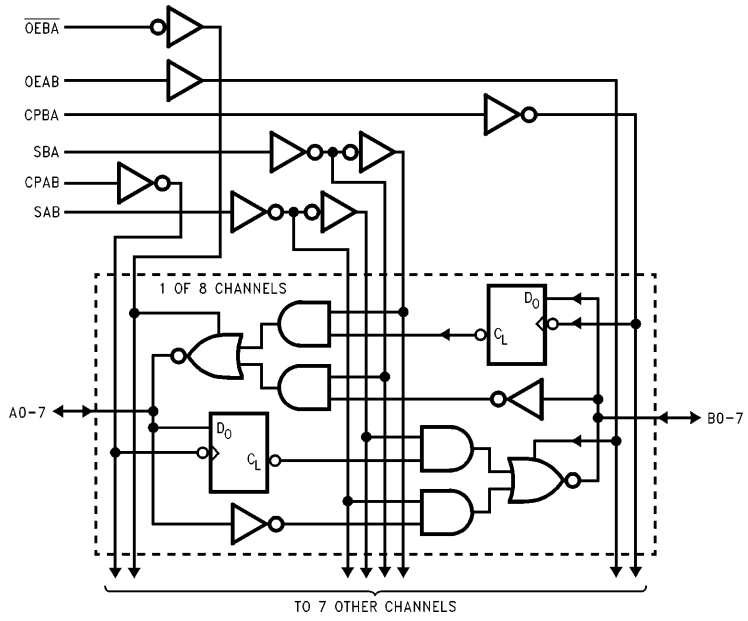
Logic Diagram



TL/F/12018–2

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

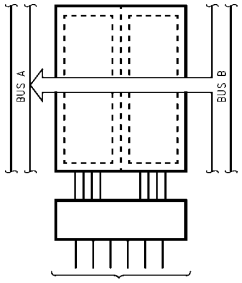
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in *Figure 1* demonstrate the four fundamental bus-management functions that can be performed with the LVT652.

Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB and $\overline{OEBA}$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

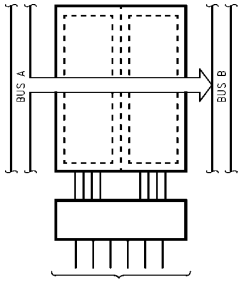
Real-Time Transfer Bus B to Bus A



TL/F/12018–3

OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

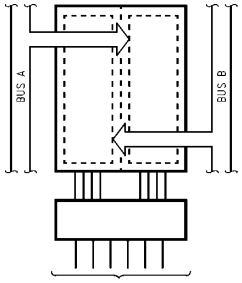
Real-Time Transfer Bus A to Bus B



TL/F/12018–4

OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

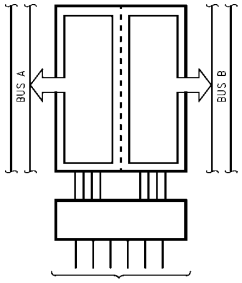
Storage



TL/F/12018–5

OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
X	H	↗	X	X	X
L	X	X	↗	X	X
L	H	↗	↗	X	X

Transfer Storage Data to A or B



TL/F/12018–6

OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

FIGURE 1

Truth Table (Note)

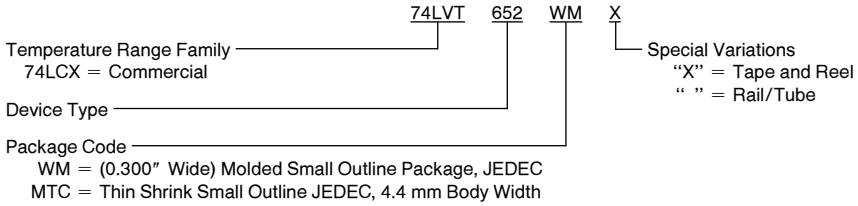
Inputs						Inputs/Outputs		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	⌐	⌐	X	X			Store A and B Data
X	H	⌐	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	⌐	⌐	X	X	Input	Output	Store A in Both Registers
L	X	H or L	⌐	X	X	Not Specified	Input	Hold A, Store B
L	L	⌐	⌐	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial ⌐ = LOW to HIGH Clock Transition

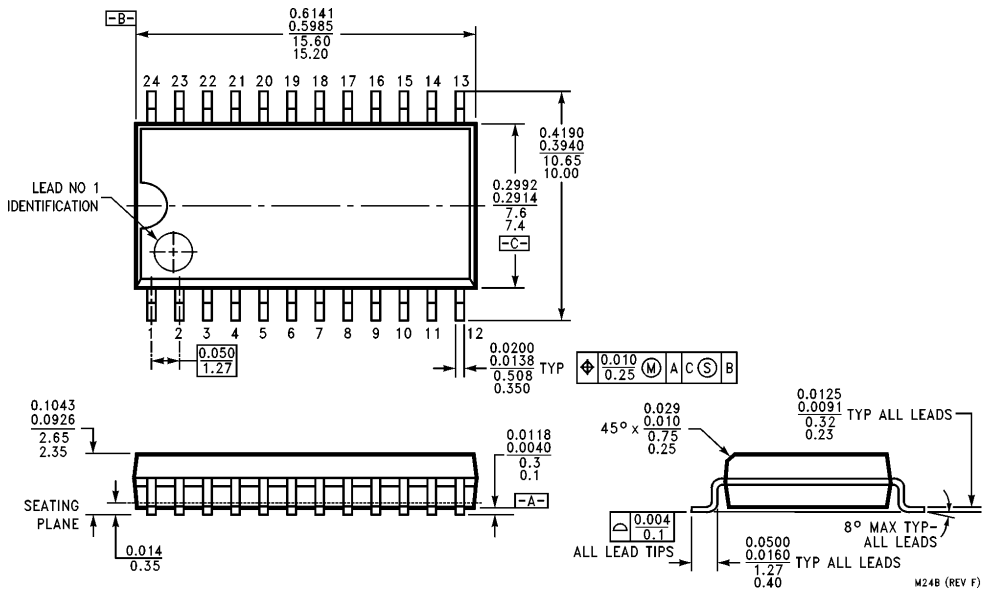
Note: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW to HIGH transition on the clock inputs.

74LVT652 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

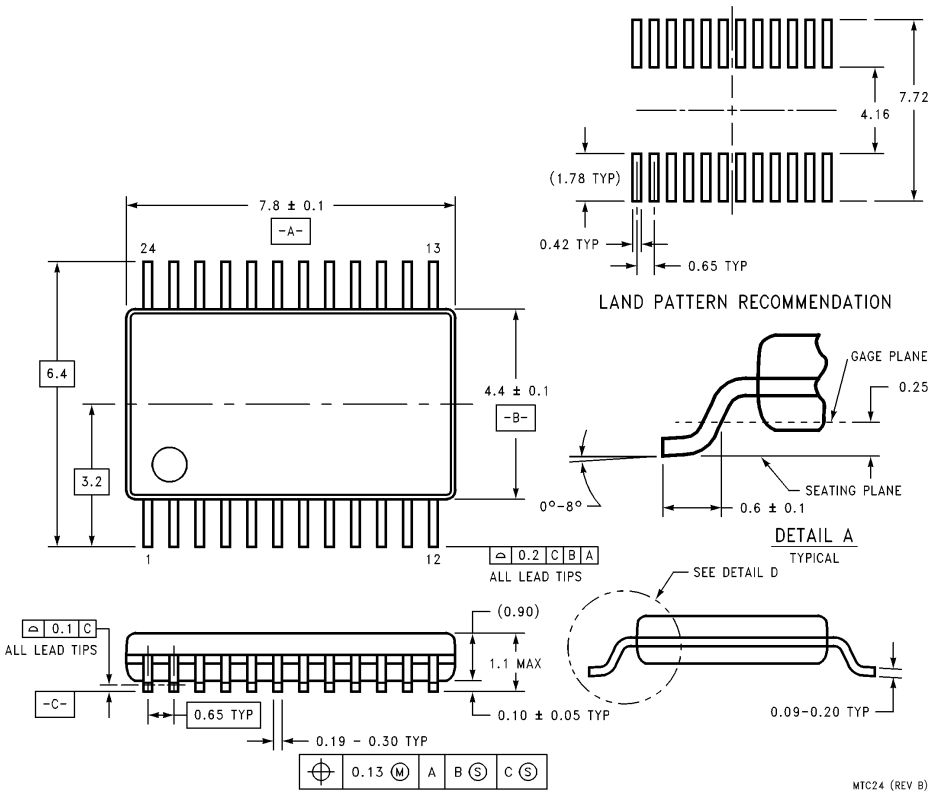


Physical Dimensions inches / millimeters



24-Lead Small Outline Integrated Circuit
Order Number 74LVT652WM or 74LVT652WMX
NS Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Molded Thin Shrink Small Outline Package, JEDEC, 6.1 mm Body Width
Order Number 74LVT652MTCX
NS Package Number MTC24

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1998
Revised January 1999

74LVTH125
Low Voltage Quad Buffer with 3-STATE Outputs

General Description

The LVTH125 contains four independent non-inverting buffers with 3-STATE outputs.

These buffers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH125 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

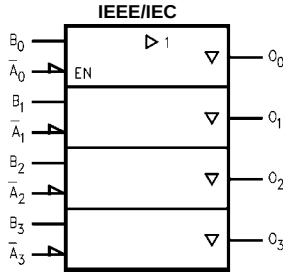
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 125
- Latch-up performance exceeds 500 mA

Ordering Code:

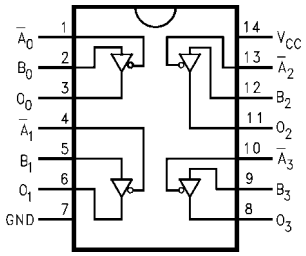
Order Number	Package Number	Package Description
74LVTH125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVTH125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{A}_n$, B_n	Inputs
O_n	3-STATE Outputs

Truth Table

Inputs		Output
$\overline{A}_n$	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$			Units	Conditions
				Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage		2.7			−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6			0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	$V_{CC} - 0.2$			V	$I_{OH} = -100$ µA
			2.7	2.4				$I_{OH} = -8$ mA
			3.0	2.0				$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage		2.7			0.2	V	$I_{OL} = 100$ µA
			2.7			0.5		$I_{OL} = 24$ mA
			3.0			0.4		$I_{OL} = 16$ mA
			3.0			0.5		$I_{OL} = 32$ mA
			3.0			0.55		$I_{OL} = 64$ mA
$I_{I(HOLD)}$	Bus-Hold Input Minimum Drive		3.0	75			µA	$V_I = 0.8V$
				−75				$V_I = 2.0V$
$I_{I(OD)}$	Bus-Hold Input Over-Drive		3.0	500			µA	(Note 4)
	Current to Change State			−500				(Note 5)
I_I	Input Current		3.6			10	µA	$V_I = 5.5V$
		Control Pins	3.6			±1		$V_I = 0V$ or V_{CC}
		Data Pins	3.6			−5		$V_I = 0V$
						1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V			±100	µA	$V_O = 0.5V$ to $3.0V$ V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6			−5	µA	$V_O = 0.5V$
I_{OZH}	3-STATE Output Leakage Current		3.6			5	µA	$V_O = 3.0V$
I_{OZH+}	3-STATE Output Leakage Current		3.6			10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled
I_{CCZ+}	Power Supply Current		3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$ Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 6)		3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

Note 4: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$					Units
		$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		
		Min	Typ (Note 9)	Max	Min	Max	
t_{PLH}	Propagation Delay Data to Output	1.0		3.5	1.0	4.5	ns
t_{PHL}		1.0		3.9	1.0	4.9	
t_{PZH}	Output Enable Time	1.0		4.0	1.0	5.5	ns
t_{PZL}		1.1		4.0	1.1	5.4	
t_{PHZ}	Output Disable Time	1.5		4.5	1.5	5.7	ns
t_{PLZ}		1.3		4.5	1.3	4.0	
t_{OSHL}	Output to Output Skew			1.0		1.0	ns
t_{OSLH}	(Note 10)						

Note 9: All typical values are at $V_{CC} = 3.3V$, $T_A = 25°C$.

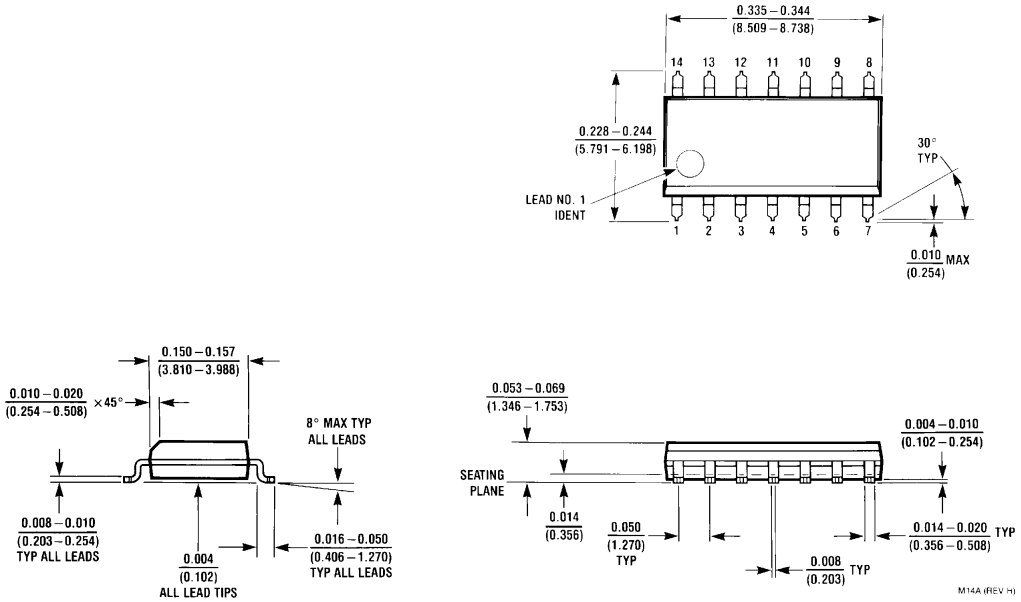
Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Capacitance (Note 11)

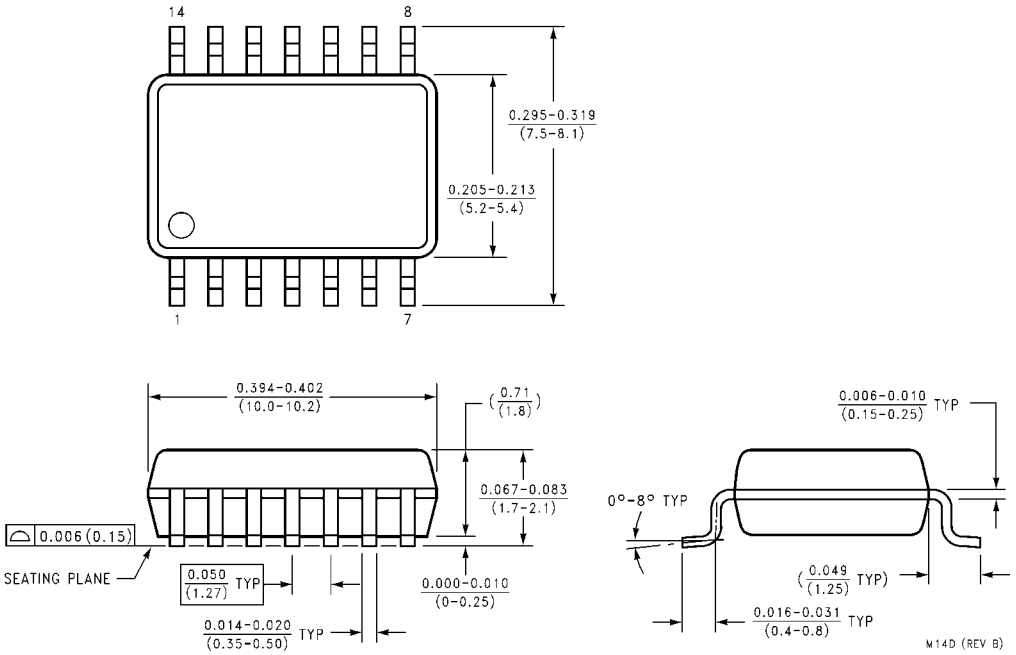
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

Note 11: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

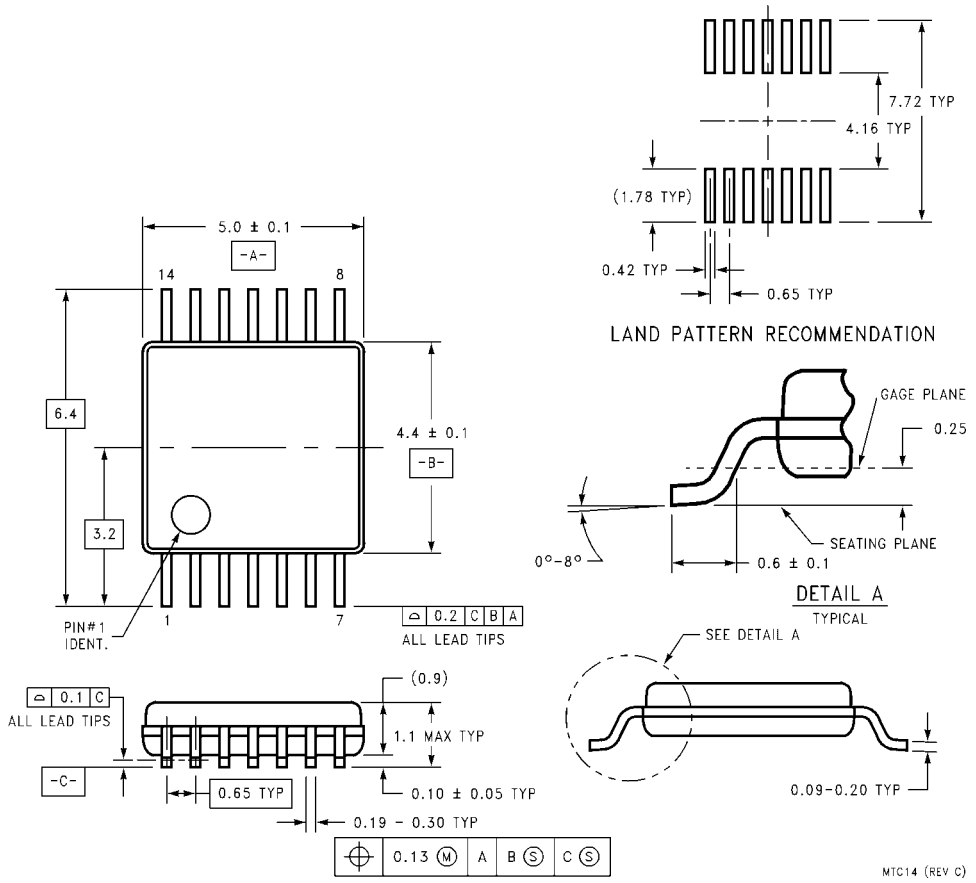


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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January 2000
Revised January 2000

74LVTH16543
Low Voltage 16-Bit Registered Transceiver with 3-STATE Outputs

General Description

The LVTH16543 16-bit transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow. Each byte has separate control inputs, which can be shorted together for full 16-bit operation.

The LVTH16543 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH16543 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

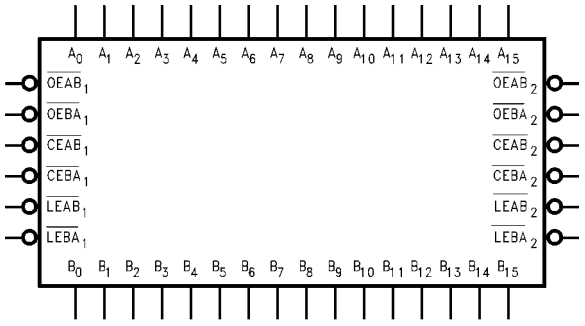
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16543
- Latch-up performance exceeds 500 mA

Ordering Code:

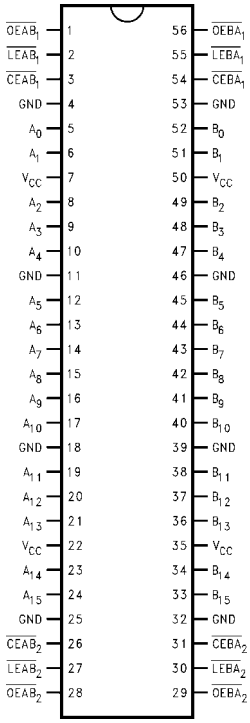
Order Number	Package Number	Package Description
74LVTH16543MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
74LVTH16543MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OEAB}_n$	A-to-B Output Enable Input (Active LOW)
$\overline{OEBA}_n$	B-to-A Output Enable Input (Active LOW)
$\overline{CEAB}_n$	A-to-B Enable Input (Active LOW)
$\overline{CEBA}_n$	B-to-A Enable Input (Active LOW)
$\overline{LEAB}_n$	A-to-B Latch Enable Input (Active LOW)
$\overline{LEBA}_n$	B-to-A Latch Enable Input (Active LOW)
A_0–A_{15}	A-to-B Data Inputs or
	B-to-A 3-STATE Outputs
B_0–B_{15}	B-to-A Data Inputs or
	A-to-B 3-STATE Outputs

Functional Description

The LVTH16543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from the A Port or take data from the B Port as indicated in the Data I/ O Control Table. With $\overline{CEAB}$ LOW, a low signal on ($\overline{LEAB}$) input makes the A to B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$. Each byte has separate control inputs, allowing the device to be used as two 8-bit transceivers or as one 16-bit transceiver.

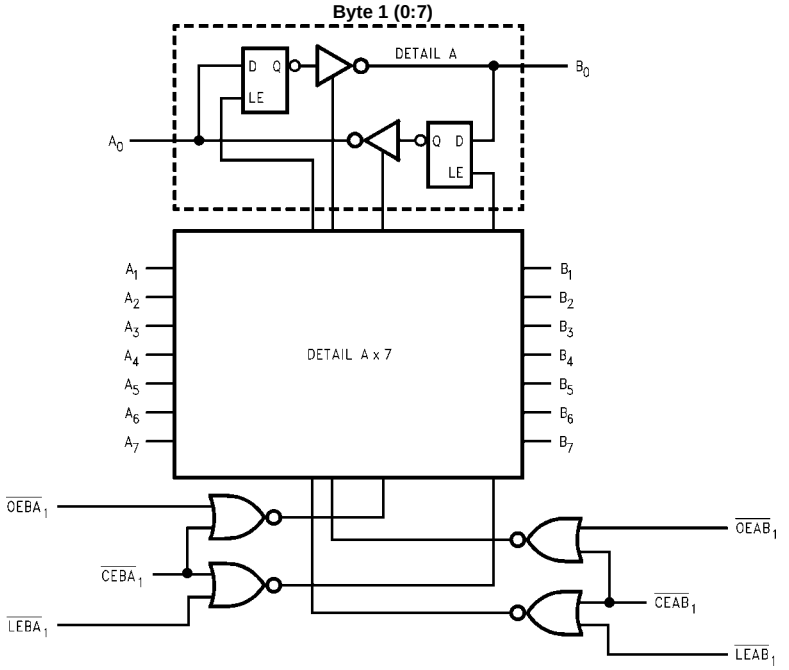
Data I/O Control Table

Inputs			Latch Status (Byte n)	Output Buffers (Byte n)
$\overline{CEAB}_n$	$\overline{LEAB}_n$	$\overline{OEAB}_n$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
A-to-B data flow shown; B-to-A flow control is the same, except using $\overline{CEBA}_n$, $\overline{LEBA}_n$ and $\overline{OEBA}_n$

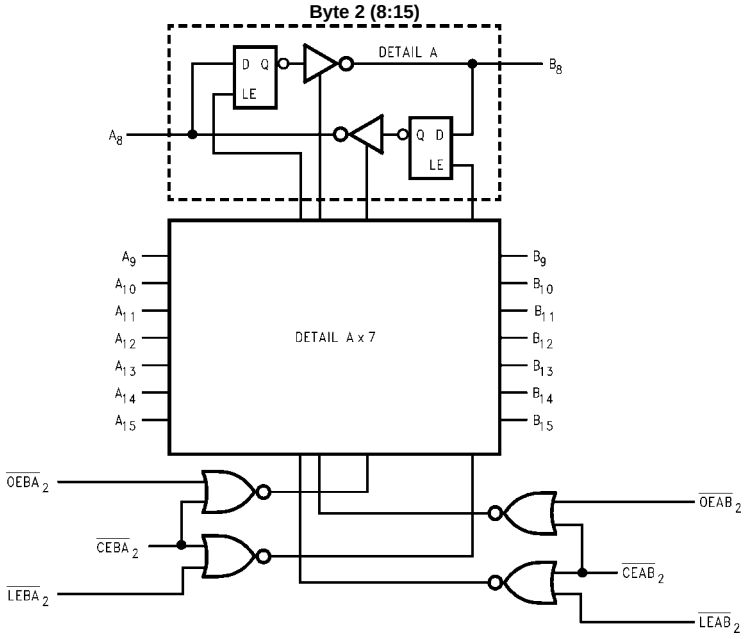
Logic Diagrams

Byte 1 (0:7)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units	Conditions
				Min	Max		
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	$V_{CC} - 0.2$		V	$I_{OH} = -100$ µA
			2.7	2.4		V	$I_{OH} = -8$ mA
			3.0	2.0		V	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	$I_{OL} = 100$ µA
			2.7		0.5	V	$I_{OL} = 24$ mA
			3.0		0.4	V	$I_{OL} = 16$ mA
			3.0		0.5	V	$I_{OL} = 32$ mA
			3.0		0.55	V	$I_{OL} = 64$ mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	$V_I = 0.8V$
				−75		µA	$V_I = 2.0V$
$I_{I(OD)}$	Bushold Input Over-Drive Current to Change State		3.0	500		µA	(Note 3)
				−500		µA	(Note 4)
I_I	Input Current		3.6		10	µA	$V_I = 5.5V$
		Control Pins	3.6		±1	µA	$V_I = 0V$ or V_{CC}
		Data Pins	3.6		−5	µA	$V_I = 0V$
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE Output Current		0–1.5V		±100	µA	$V_O = 0.5V$ to $3.0V$ V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	$V_O = 0.0V$
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	$V_O = 3.6V$
I_{OZH+}	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
I_{CCZ+}	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 5)		3.6		0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND

Note 3: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 4: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 5: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 6)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions
			Min	Typ	Max		$C_L = 50$ pF, $R_L = 500\Omega$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 7)

Note 6: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 7: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\ \Omega$				Units
			$V_{CC} = 3.3 \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
t_{PLH}	Propagation Delay		1.2	4.2	1.2	4.5	ns
t_{PHL}	Data to Outputs		1.2	4.4	1.2	4.9	
t_{PLH}	Propagation Delay		1.3	4.7	1.3	5.5	ns
t_{PHL}	$\overline{LE}$ to A or B		1.3	5.1	1.3	5.8	
t_{PZH}	Output Enable Time		1.3	4.7	1.3	5.4	ns
t_{PZL}	$\overline{OE}$ to A or B		1.3	5.1	1.3	6.1	
t_{PHZ}	Output Disable Time		2.0	5.5	2.0	5.7	ns
t_{PLZ}	$\overline{OE}$ to A or B		2.0	4.9	2.0	4.9	
t_{PZH}	Output Enable Time		1.3	4.6	1.3	5.6	ns
t_{PZL}	$\overline{CE}$ to A or B		1.3	5.0	1.3	6.1	
t_{PHZ}	Output Disable Time		2.0	5.5	2.0	5.8	ns
t_{PLZ}	$\overline{CE}$ to A or B		2.0	4.9	2.0	4.9	
t_W	Pulse Duration	$\overline{LE}$ LOW	3.3		3.3		ns
t_S	Setup Time	A or B before $\overline{LE}$, Data HIGH	0.5		0.5		ns
		A or B before $\overline{LE}$, Data LOW	0.8		1.3		
		A or B before $\overline{CE}$, Data HIGH	0.5		0.0		
		A or B before $\overline{CE}$, Data LOW	0.6		1.1		
t_H	Hold Time	A or B after $\overline{LE}$, Data HIGH	1.5		0.7		ns
		A or B after $\overline{LE}$, Data LOW	1.2		1.3		
		A or B after $\overline{CE}$, Data HIGH	1.7		0.9		
		A or B after $\overline{CE}$, Data LOW	1.6		1.8		
t_{OSLH}	Output to Output Skew (Note 8)			1.0		1.0	ns
t_{OSHL}				1.0		1.0	

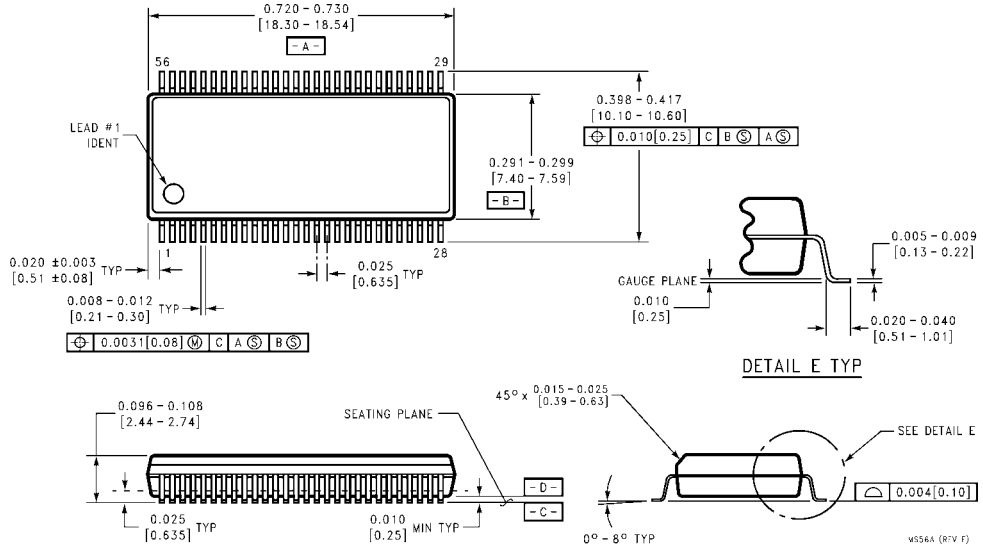
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 9)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = OPEN, V_I = 0V or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	V_{CC} = 3.0V, V_O = 0V or V_{CC}	8	pF

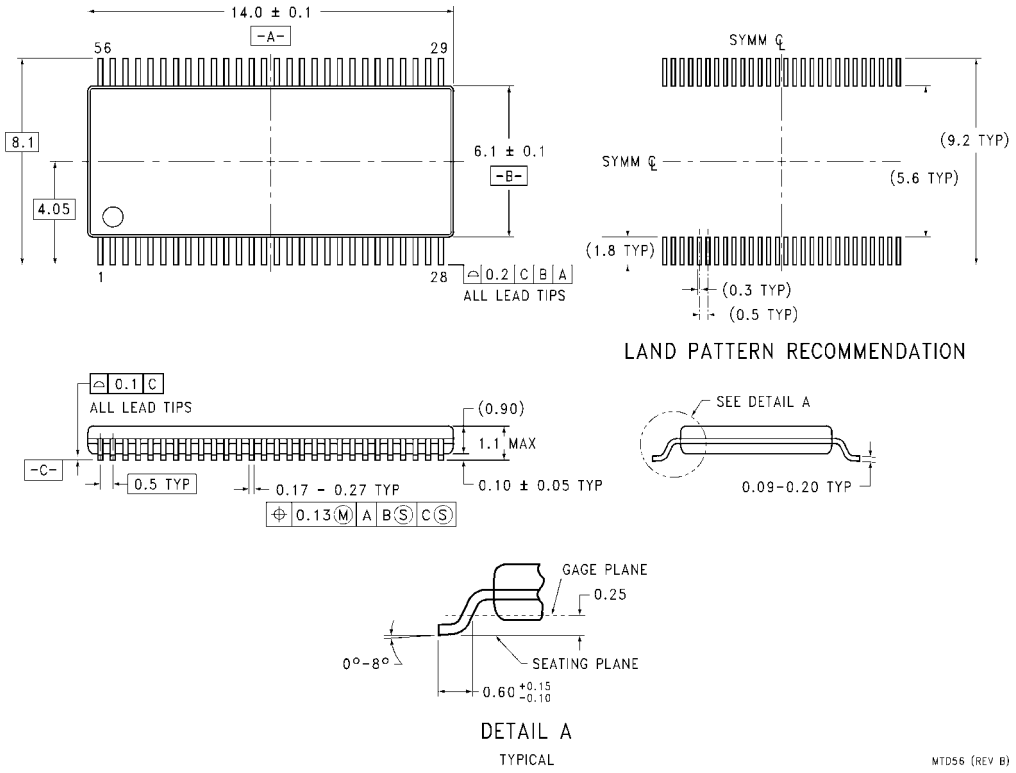
Note 9: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74LVTH16646
Low Voltage 16-Bit Transceiver/Register with 3-STATE Outputs

General Description

The LVTH16646 contains sixteen non-inverting bidirectional registered bus transceivers providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition (see Functional Description).

The LVTH16646 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH16646 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

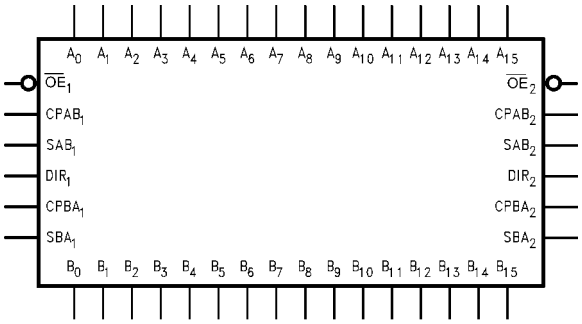
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16646
- Latch-up performance exceeds 500 mA

Ordering Code:

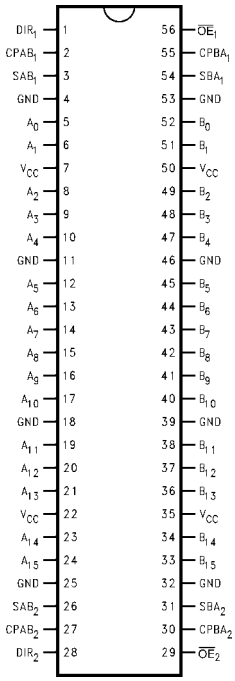
Order Number	Package Number	Package Description
74LVTH16646MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
74LVTH16646MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_{15}	Data Register A Inputs/3-STATE Outputs
B_0–B_{15}	Data Register B Inputs/3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Inputs
DIR_n	Direction Control Inputs

Truth Table(Note 1)

Inputs						Data I/O		Output Operation Mode
$\overline{OE}_1$	DIR_1	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_{0-7}	B_{0-7}	
H	X	H or L	H or L	X	X			Isolation
H	X	↗	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↗	X	X			Clock B_n Data Into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↗	X	L	X	Input	Output	Clock A_n Data to A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↗	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↗	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↗	X	H			Clock B_n into B Register and Output to A_n

H = HIGH Voltage Level
X = Immaterial
L = LOW Voltage Level
↗ = LOW-to-HIGH Transition.

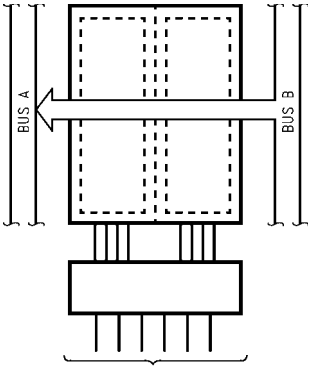
Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

Functional Description

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both. The select (SAB_n, SBA_n) controls can multiplex stored and real-time. The examples shown below demonstrate the four fundamental bus-management functions that can be performed.

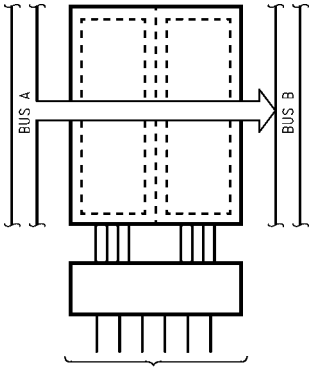
The direction control (DIR_n) determines which bus will receive data when $\overline{OE}_n$ is LOW. In the isolation mode ($\overline{OE}_n$ HIGH), A data may be stored in one register and/or B data may be stored in the other register. When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two busses, A or B, may be driven at a time.

Real-Time Transfer
Bus B to Bus A



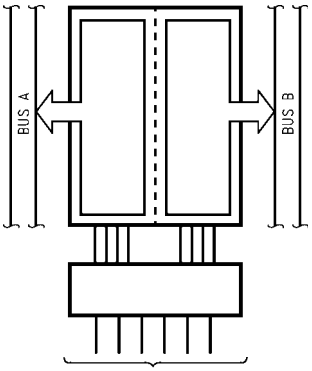
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Real-Time Transfer
Bus A to Bus B



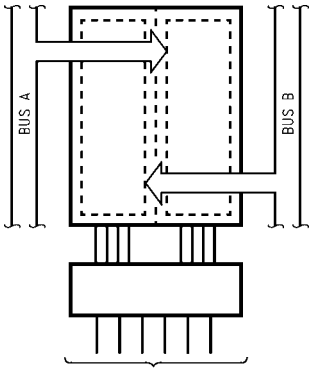
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	X	X	L	X

Transfer Storage
Data to A or B



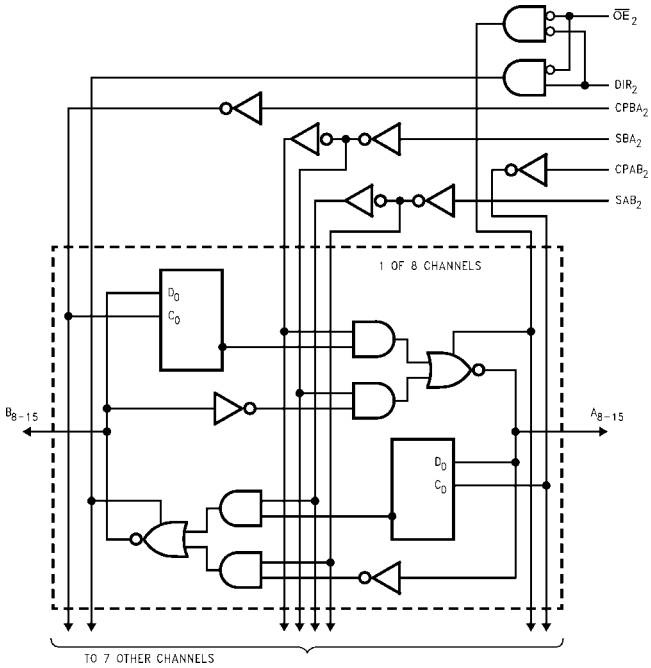
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	H or L	X	H
L	H	H or L	X	H	X

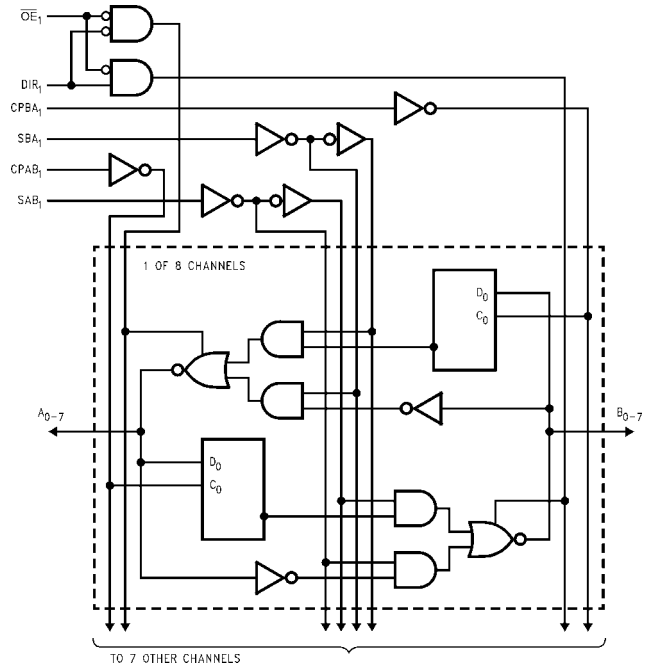
Storage



$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	↑	X	L	X
L	L	X	↑	X	L
H	X	↑	X	X	X
H	X	X	↑	X	X

Logic Diagrams





Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 3: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units	Conditions
				Min	Max		
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 µA
			2.7	2.4		V	I_{OH} = −8 mA
			3.0	2.0		V	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5	V	I_{OL} = 24 mA
			3.0		0.4	V	I_{OL} = 16 mA
			3.0		0.5	V	I_{OL} = 32 mA
			3.0		0.55	V	I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
				−75		µA	V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive Current to Change State		3.0	500		µA	(Note 4)
				−500		µA	(Note 5)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6		−5	µA	V_I = 0V
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE Output Current		0–1.5V		±100	µA	V_O = 0.5V to 3.0V V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.6V
$I_{OZH}+$	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current (Note 6)		3.6		0.2	mA	One Input at V_{CC} − 0.6V Other Inputs at V_{CC} or GND

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions C_L = 50 pF, R_L = 500Ω
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
			$V_{CC} = 3.3 \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		150		150		MHz
t_{PLH}	Propagation Delay		1.3	5.4	1.3	5.9	ns
t_{PHL}	CPAB or CPBA to A or B		1.3	5.2	1.3	5.8	
t_{PLH}	Propagation Delay		1.0	4.4	1.0	4.7	ns
t_{PHL}	Data to A or B		1.0	4.6	1.0	5.1	
t_{PLH}	Propagation Delay		1.0	4.6	1.0	5.4	ns
t_{PHL}	SBA or SAB to A or B		1.0	4.8	1.0	5.6	
t_{PZH}	Output Enable Time		1.0	4.7	1.0	5.4	ns
t_{PZL}	$\overline{OE}$ to A or B		1.0	5.1	1.0	6.0	
t_{PHZ}	Output Disable Time		2.0	5.6	2.0	6.1	ns
t_{PLZ}	$\overline{OE}$ to A or B		2.0	5.4	2.0	6.1	
t_{PZH}	Output Enable Time		1.0	4.9	1.0	5.4	ns
t_{PZL}	DIR to A or B		1.0	5.4	1.0	6.4	
t_{PHZ}	Output Disable Time		1.5	6.4	1.5	7.1	ns
t_{PLZ}	DIR to A or B		1.5	5.4	1.5	5.9	
t_W	Pulse Duration	CPAB or CPBA HIGH or LOW	3.3		3.3		ns
t_S	Setup Time	A or B before CPAB or CPBA, Data HIGH	1.2		1.5		ns
		A or B before CPAB or CPBA, Data LOW	2.0		2.8		
t_H	Hold Time	A or B after CPAB or CPBA, Data HIGH	0.5		0.0		ns
		A or B after CPAB or CPBA, Data LOW	0.5		0.5		
t_{OSHL}	Output to Output Skew (Note 9)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

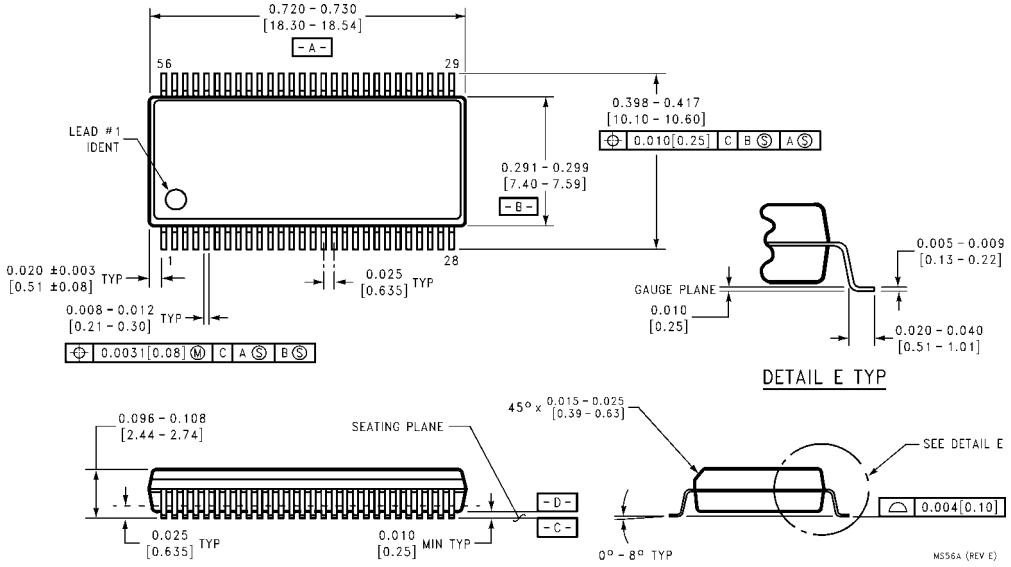
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 10)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	V_{CC} = 3.0V, V_O = 0V or V_{CC}	8	pF

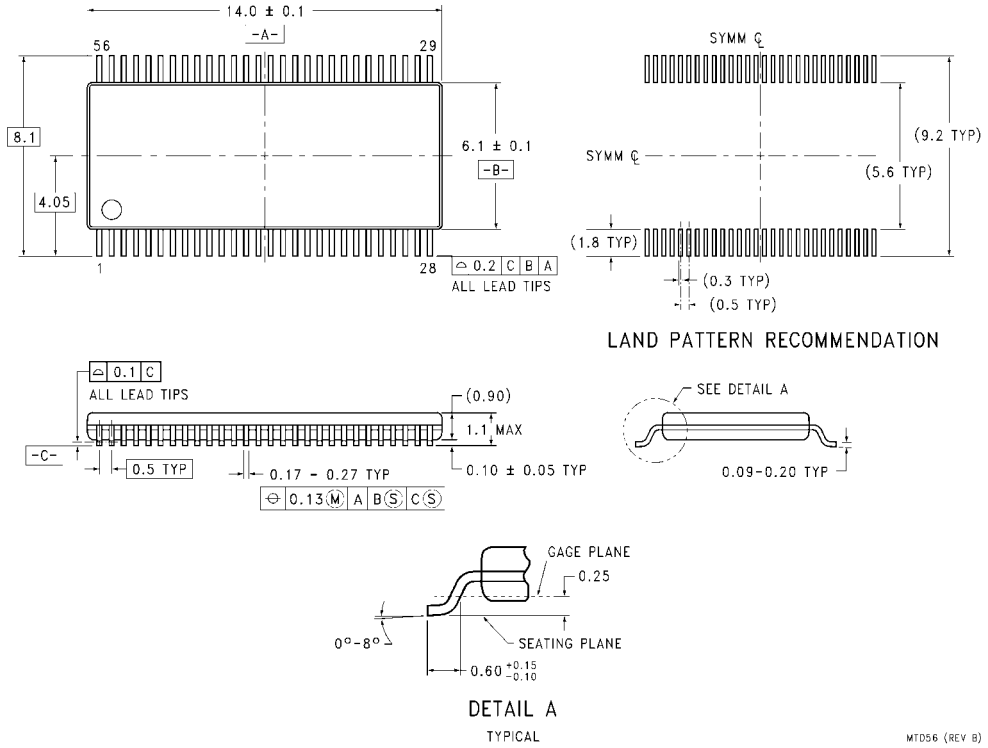
Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74LVTH16652
Low Voltage 16-Bit Transceiver/Register with 3-STATE Outputs

General Description

The LVTH16652 consists of sixteen bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to the HIGH logic level. Output Enable pins (OEAB, $\overline{OEBA}$) are provided to control the transceiver function (see Functional Description).

The LVTH16652 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

The transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH16652 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

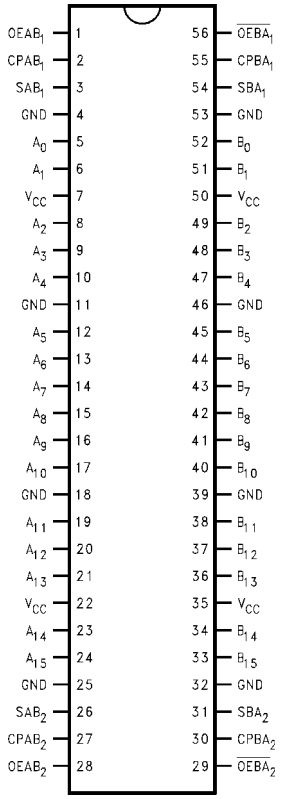
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16652
- Latch-up performance exceeds 500 mA

Ordering Code:

Order Number	Package Number	Package Description
74LVTH16652MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
74LVTH16652MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_{15}	Data Register A Inputs/ 3-STATE Outputs
B_0–B_{15}	Data Register B Inputs/ 3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
SAB_n, SBA_n	Select Inputs
$OEAB_n$, $\overline{OEBA}_n$	Output Enable Inputs

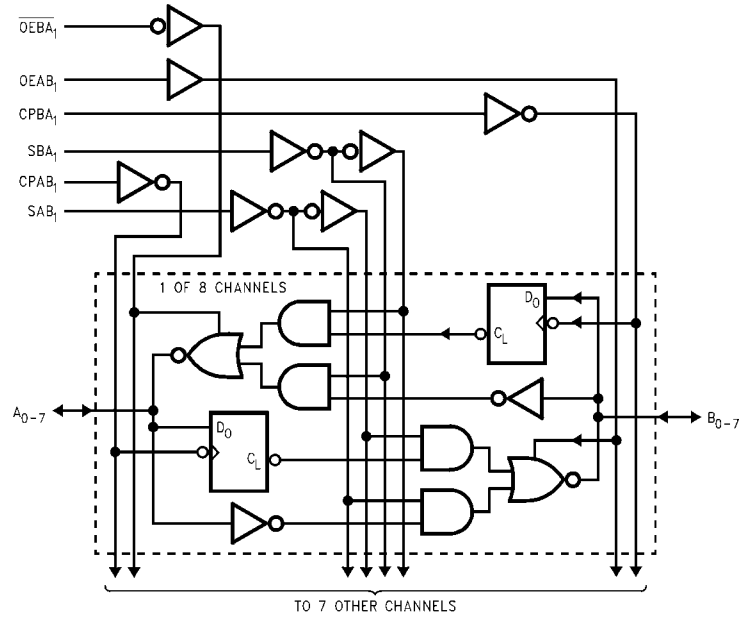
Truth Table (Note 1)

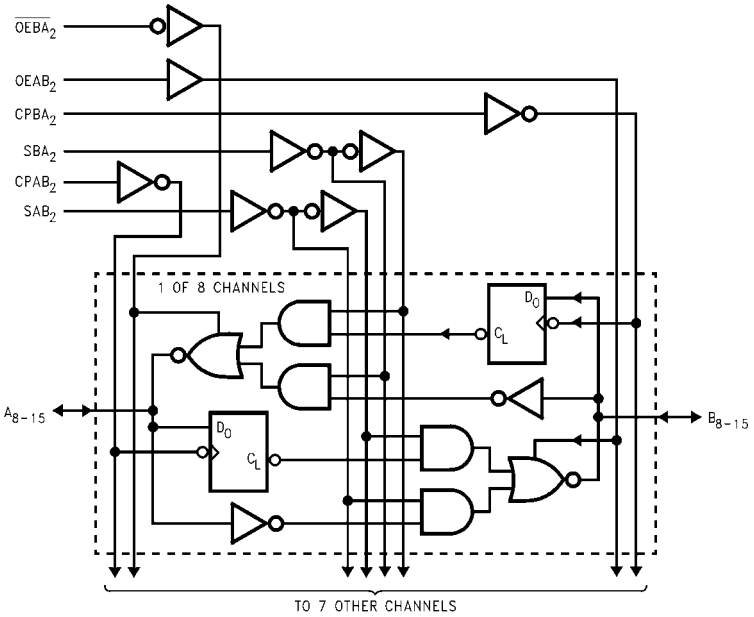
Inputs						Inputs/Outputs		Operating Mode
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	↑	↑	X	X			Store A and B Data
X	H	↑	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	↑	↑	X	X	Input	Output	Store A in Both Registers
L	X	H or L	↑	X	X	Not Specified	Input	Hold A, Store B
L	L	↑	↑	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial ↑ = LOW-to-HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs. This also applies to data I/O (A and B: 8–15) and #2 control pins

Logic Diagrams





Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

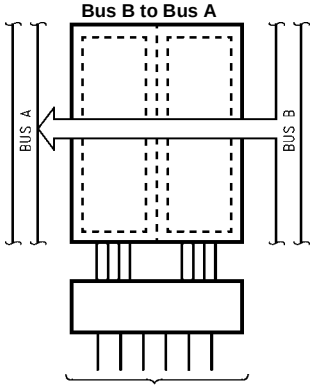
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB_n, SBA_n) controls can multiplex stored and real-time.

The examples below demonstrate the four fundamental bus-management functions that can be performed with the LVTH16652.

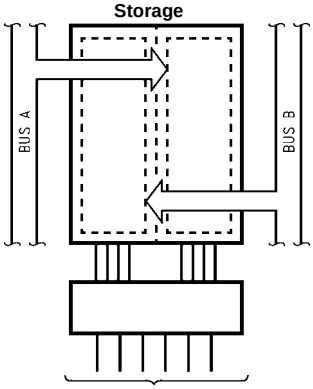
Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW-to-HIGH transitions at the appropriate Clock Inputs ($CPAB_n$, $CPBA_n$) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling $OEAB_n$ and $\overline{OEBA}_n$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Real-Time Transfer
Bus B to Bus A



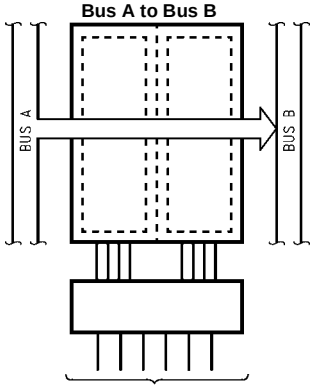
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
L	L	X	X	X	L

Storage



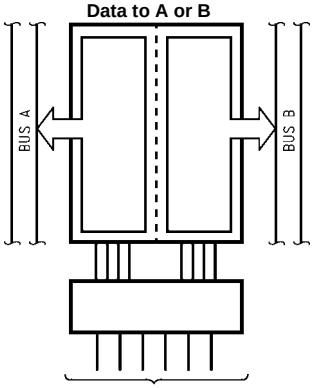
$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
X	H	⌐	X	X	X
L	X	X	⌐	X	X
L	H	⌐	⌐	X	X

Real-Time Transfer
Bus A to Bus B



$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
H	H	X	X	L	X

Transfer Storage
Data to A or B



$OEAB_1$	$\overline{OEBA}_1$	$CPAB_1$	$CPBA_1$	SAB_1	SBA_1
H	L	H or L	H or L	H	H

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 3: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$ Min	Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or $V_O \ge V_{CC} - 0.1V$
V_{IL}	Input LOW Voltage		2.7–3.6		0.8	V	
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 µA
			2.7	2.4			I_{OH} = −8 mA
			3.0	2.0			I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5		I_{OL} = 24 mA
			3.0		0.4		I_{OL} = 16 mA
			3.0		0.5		I_{OL} = 32 mA
			3.0		0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
				−75			V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive		3.0	500		µA	(Note 4)
	Current to Change State			−500			(Note 5)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1		V_I = 0V or V_{CC}
		Data Pins	3.6		−5		V_I = 0V
					1		$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE		0–1.5V		±100	µA	V_O = 0.5V to 3.0V
	Output Current						V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.6V
I_{OZH+}	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
I_{CCZ+}	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current		3.6		0.2	mA	One Input at V_{CC} − 0.6V
	(Note 6)						Other Inputs at V_{CC} or GND

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Min	Typ	Max	Units	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
			$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		150		150		MHz
t_{PHL}	Propagation Delay		1.3	4.8	1.3	5.4	ns
t_{PLH}	CPAB or CPBA to A or B		1.3	5.1	1.3	5.6	
t_{PHL}	Propagation Delay		1.0	4.5	1.0	5.1	ns
t_{PLH}	Data to A or B		1.0	4.4	1.0	4.7	
t_{PHL}	Propagation Delay		1.0	4.9	1.0	5.5	ns
t_{PLH}	SBA or SAB to A or B		1.0	4.8	1.0	5.4	
t_{PZL}	Output Enable Time		1.0	4.9	1.0	5.8	ns
t_{PZH}	$\overline{OE}$ to A		1.0	4.8	1.0	5.8	
t_{PLZ}	Output Disable Time		1.6	5.6	1.6	6.1	ns
t_{PHZ}	$\overline{OE}$ to A		2.0	5.4	2.0	6.1	
t_{PZL}	Output Enable Time		1.3	5.0	1.3	5.4	ns
t_{PZH}	OE to B		1.3	4.8	1.3	5.4	
t_{PLZ}	Output Disable Time		1.3	5.5	1.3	6.2	ns
t_{PHZ}	OE to B		1.3	5.6	1.3	6.3	
t_S	Setup Time	A or B before CPAB or CPBA, Data HIGH	1.2		1.5		ns
		A or B before CPAB or CPBA, Data LOW	2.0		2.8		
t_H	Hold Time	A or B before CPAB or CPBA, Data HIGH	0.5		0.0		ns
		A or B before CPAB or CPBA, Data LOW	0.5		0.5		
t_W	Pulse Width	CPAB or CPBA HIGH or LOW	3.3		3.3		ns
t_{OSHL}	Output to Output Skew (Note 9)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

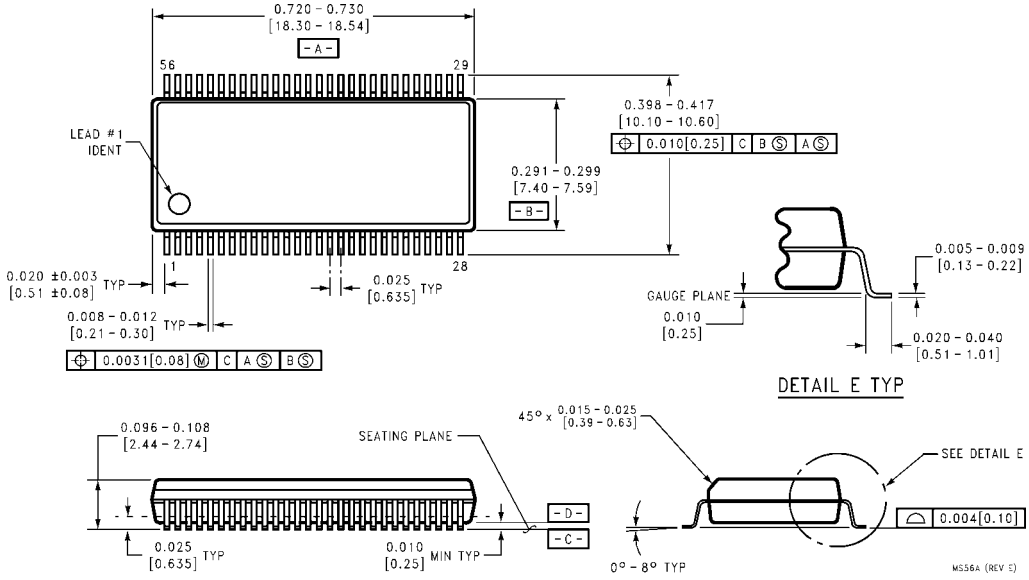
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 10)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	V_{CC} = 3.0V, V_O = 0V or V_{CC}	8	pF

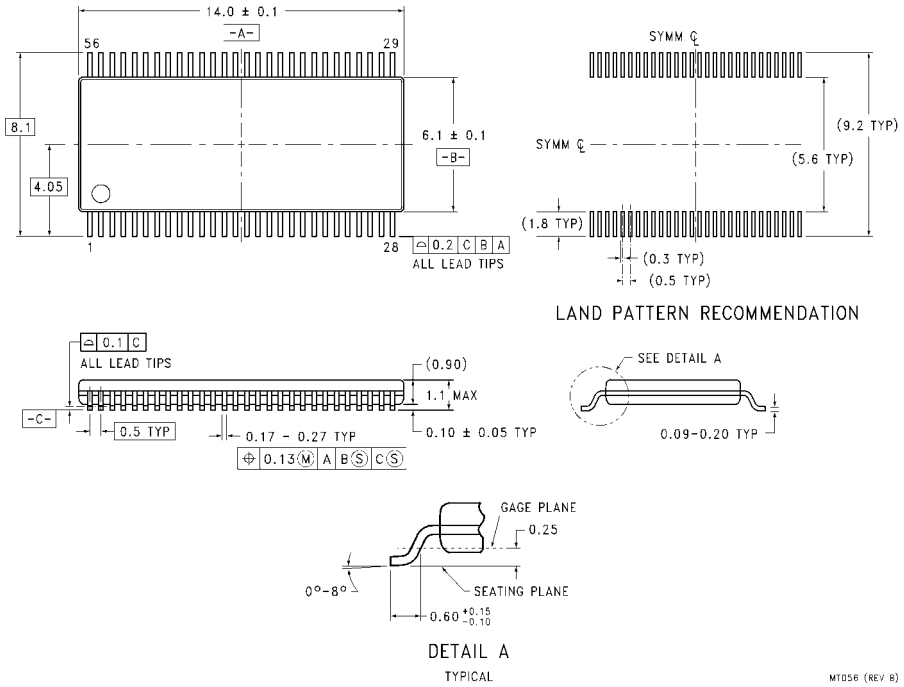
Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74LVTH16952
Low Voltage 16-Bit Registered Transceiver with 3-STATE Outputs

General Description

The LVTH16952 is a 16-bit registered transceiver. Two 8-bit back to back registers store data flowing in both directions between two bidirectional buses. Separate clock, clock enable, and output enable signals are provided for each register.

The LVTH16952 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

The registered transceiver is designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment.

The LVTH16952 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

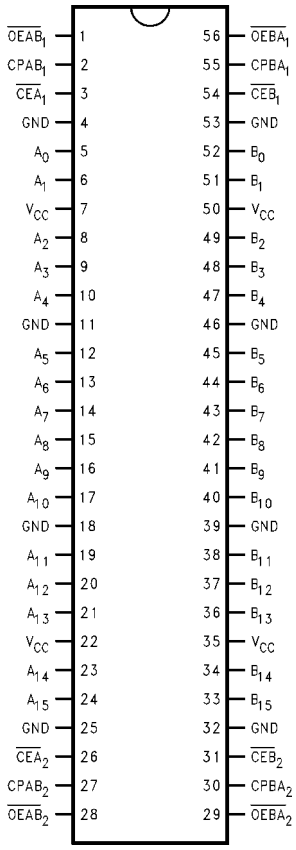
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 16952
- Latch-up performance exceeds 500 mA

Ordering Code:

Order Number	Package Number	Package Description
74LVTH16952MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
74LVTH16952MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_{16}	Data Register A Inputs B-Register 3-STATE Outputs
B_0–B_{16}	Data Register B Inputs A-Register 3-STATE Outputs
$CPAB_n$, $CPBA_n$	Clock Pulse Inputs
$\overline{CEA}_n$, $\overline{CEB}_n$	Clock Enable
$\overline{OEAB}_n$, $\overline{OEBA}_n$	Output Enable Inputs

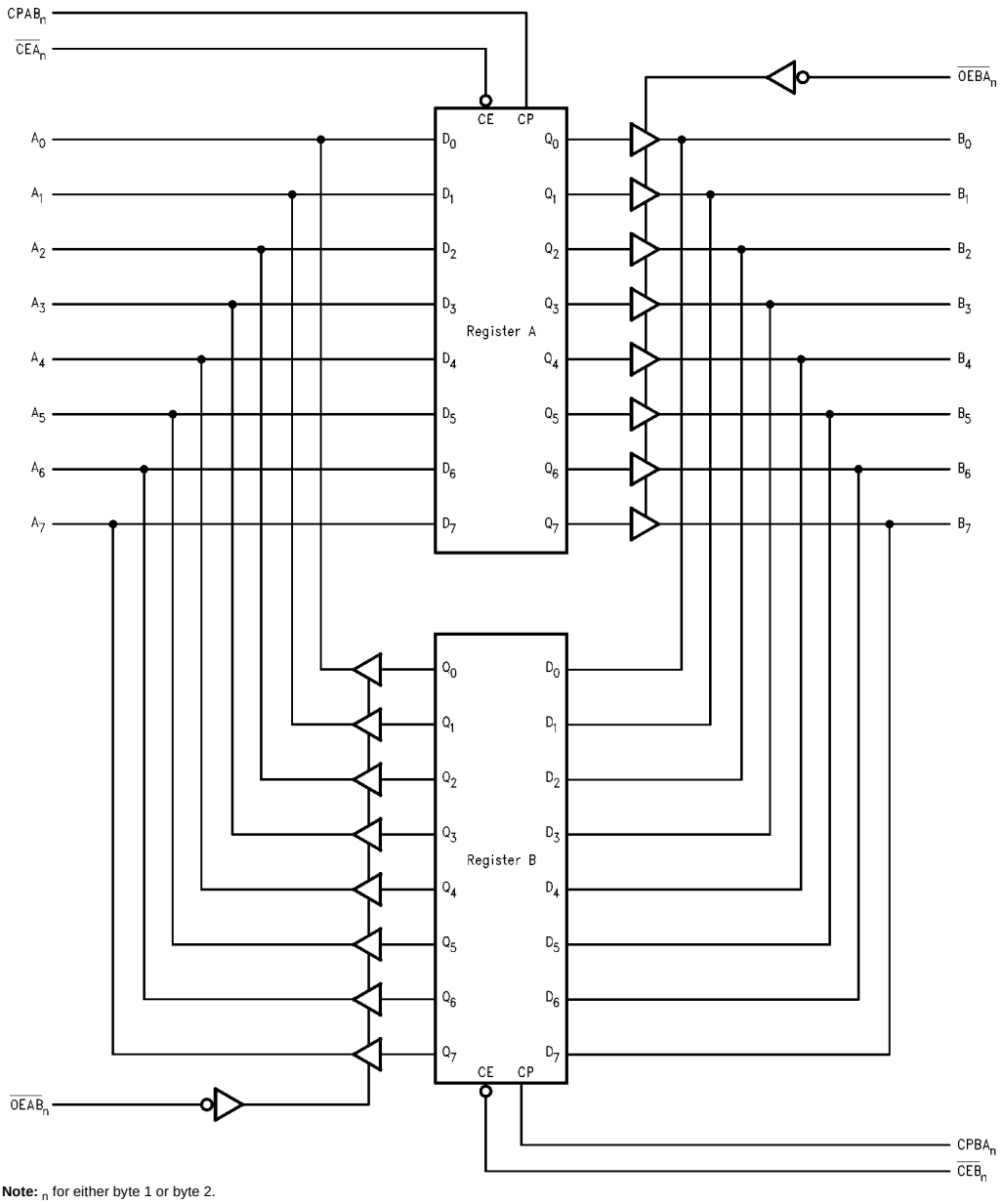
Truth Table(Note 1)

Inputs				Internal Register	Output
A_n	$CPAB_n$	$\overline{CEA}_n$	$\overline{OEAB}_n$	Value	B_n
X	X	H	L	NC	B_0
X	X	H	H	NC	Z
L	⌐	L	L	L	L
L	⌐	L	H	L	Z
H	⌐	L	L	H	H
H	⌐	L	H	H	Z
X	L	X	L	NC	B_0
X	H	X	L	NC	B_0
X	L	X	H	NC	Z
X	H	X	H	NC	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = Output High Impedance
⌐ = LOW-to-HIGH Transition.
NC = No Change (state established by last valid CP)
B_0 = State established by last valid CP

Note 1: A to B data flow shown; B to A flow control is the same, but used $\overline{OEBA}_n$, $CPBA_n$ and $\overline{CEB}_n$.

Logic Diagram



Note: $_n$ for either byte 1 or byte 2.

Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH-Level Output Current		−32	mA
I_{OL}	LOW-Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	+85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 3: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$ Min	Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	$I_I = -18$ mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	$V_{CC} - 0.2$		V	$I_{OH} = -100$ µA
			2.7	2.4		V	$I_{OH} = -8$ mA
			3.0	2.0		V	$I_{OH} = -32$ mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	$I_{OL} = 100$ µA
			2.7		0.5	V	$I_{OL} = 24$ mA
			3.0		0.4	V	$I_{OL} = 16$ mA
			3.0		0.5	V	$I_{OL} = 32$ mA
			3.0		0.55	V	$I_{OL} = 64$ mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	$V_I = 0.8V$
				−75		µA	$V_I = 2.0V$
$I_{I(OD)}$	Bushold Input Over-Drive		3.0	500		µA	(Note 4)
	Current to Change State			−500		µA	(Note 5)
I_I	Input Current		3.6		10	µA	$V_I = 5.5V$
		Control Pins	3.6		±1	µA	$V_I = 0V$ or V_{CC}
		Data Pins	3.6		−5	µA	$V_I = 0V$
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE		0–1.5V		±100	µA	$V_O = 0.5V$ to $3.0V$
	Output Current						V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	$V_O = 0.0V$
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	$V_O = 3.6V$
$I_{OZH}+$	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs High
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs Low
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$,
							Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current		3.6		0.2	mA	One Input at $V_{CC} - 0.6V$
	(Note 6)						Other Inputs at V_{CC} or GND

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Min	Typ	Max	Units	Conditions $C_L = 50$ pF, $R_L = 500\Omega$
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
			$V_{CC} = 3.3 \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		150		150		MHz
t_{PLH}	Propagation Delay		1.3	4.4	1.3	4.7	ns
t_{PHL}	CPBA or CPAB to A or B		1.3	4.8	1.3	5.0	
t_{PZH}	Output Enable Time		1.0	4.3	1.0	4.9	ns
t_{PZL}	$\overline{OE}$ to A or B		1.0	4.8	1.0	5.7	
t_{PHZ}	Output Disable Time		2.1	5.7	2.1	6.2	ns
t_{PLZ}	$\overline{OE}$ to A or B		2.1	5.1	2.1	5.3	
t_W	Pulse Width, CPAB or CPBA HIGH or LOW		3.3		3.3		ns
t_S	Setup Time	A or B before CPAB or CPBA	1.7		2.5		ns
		$\overline{CEA}$ or $\overline{CEB}$ before CPAB or CPBA	2.0		2.8		
t_H	Hold Time	A or B after CPAB or CPBA	0.8		0.0		ns
		$\overline{CEA}$ or $\overline{CEB}$ after CPAB or CPBA	0.4		0.0		
t_{OSLH}	Output to Output Skew (Note 9)			1.0		1.0	ns
t_{OSHL}				1.0		1.0	

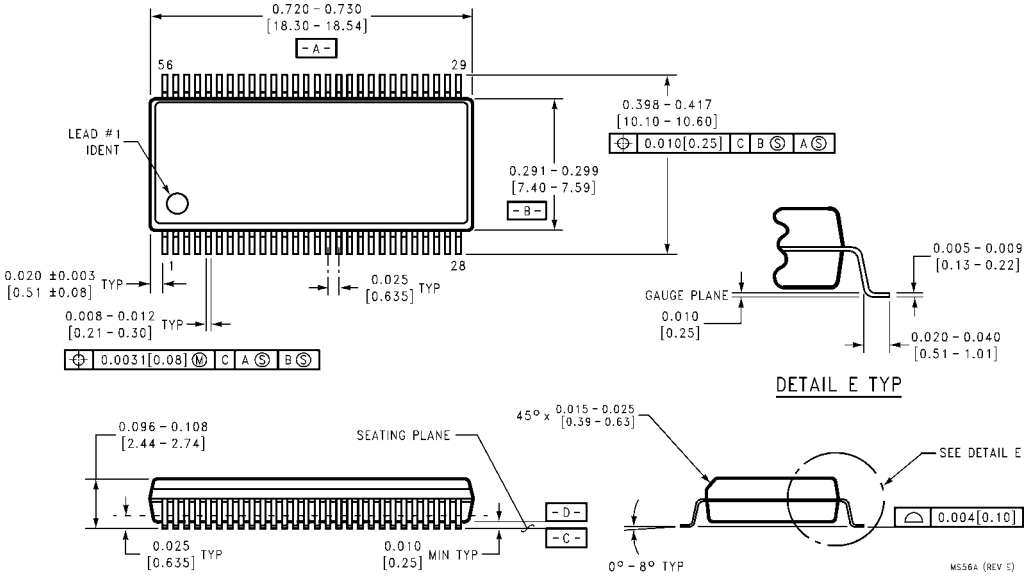
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 10)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = OPEN, V_I = 0V or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	V_{CC} = 3.0V, V_O = 0V or V_{CC}	8	pF

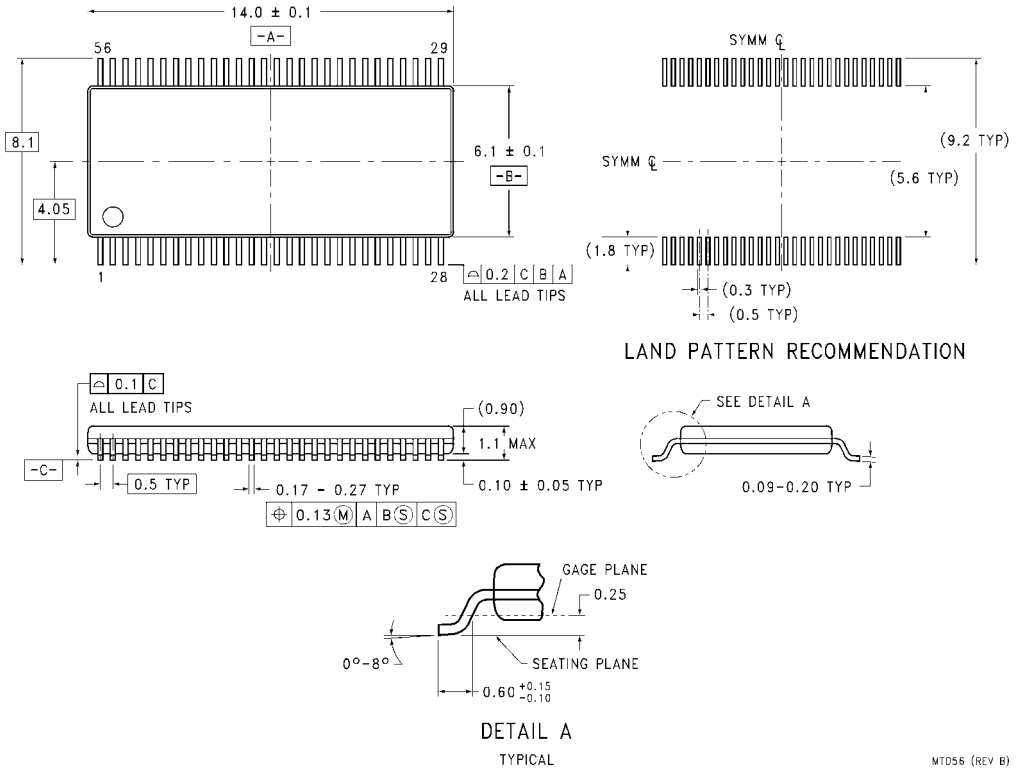
Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS56A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised July 1999

74LVTH273
Low Voltage Octal D-Type Flip-Flop with Clear

General Description

The LVTH273 is a high-speed, low-power positive-edge-triggered octal D-type flip-flop featuring separate D-type inputs for each flip-flop. A buffered Clock (CP) and Clear ($\overline{CLR}$) are common to all flip-flops.

The state of each D-type input, one setup time before the positive clock transition, is transferred to the corresponding flip-flop's output.

The LVTH273 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal flip-flops are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH273 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

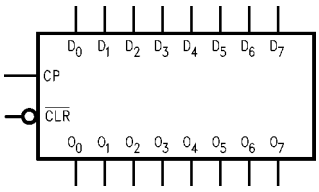
- Input and output interface capability to systems at 5V V_{CC}
- Bushold on the data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 273
- Latch-up performance exceeds 500 mA

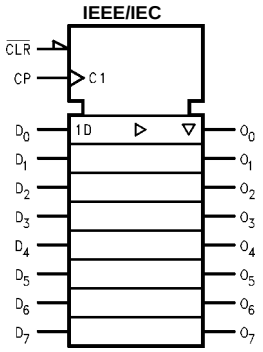
Ordering Code:

Order Number	Package Number	Package Description
74LVTH273WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
74LVTH273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

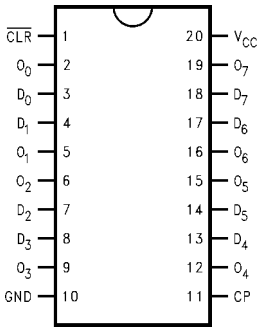
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{CLR}$	Clear
O_0–O_7	Outputs

Truth Table

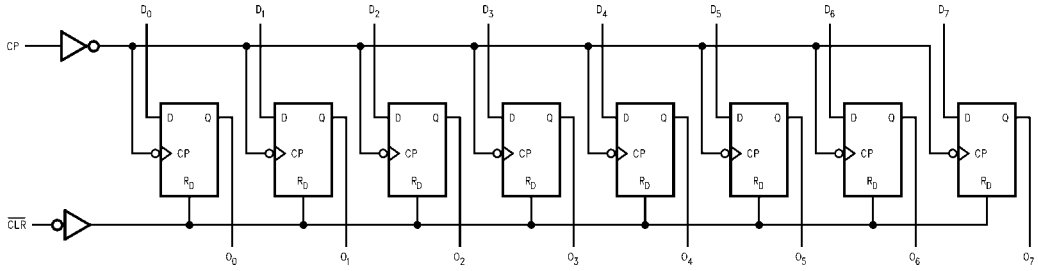
Inputs			Outputs
D_n	CP	$\overline{CLR}$	O_n
H	⌐	H	H
L	⌐	H	L
X	H or L	H	O_o
X	X	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition
O_o = Previous O_o before HIGH-to-LOW of CP

Functional Description

The LVTH273 consists of eight positive-edge-triggered flip-flops with individual D-type inputs. The buffered Clock and Clear are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. When the Clock is either HIGH or LOW, the D-input signal has no effect at the output. When the Clear ($\overline{CLR}$) is LOW, all Outputs will be forced LOW.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	−50	$V_O < GND$	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = −40°C to +85°C			Units	Conditions
			Min	Typ (Note 3)	Max		
V_{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage	2.7–3.6			0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage	2.7–3.6	V_{CC} − 0.2			V	I_{OH} = −100 µA
		2.7	2.4				I_{OH} = −8 mA
		3.0	2.0				I_{OH} = −32 mA
V_{OL}	Output LOW Voltage	2.7			0.2	V	I_{OL} = 100 µA
		2.7			0.5		I_{OL} = 24 mA
		3.0			0.4		I_{OL} = 16 mA
		3.0			0.5		I_{OL} = 32 mA
		3.0			0.55		I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive	3.0	75			µA	V_I = 0.8V
			−75				V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive	3.0	500			µA	(Note 4)
	Current to Change State		−500				(Note 5)
I_I	Input Current	3.6			10	µA	V_I = 5.5V
	Control Pins	3.6			±1	µA	V_I = 0V or V_{CC}
	Data Pins	3.6			−5	µA	V_I = 0V
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current	0			±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
I_{CCH}	Power Supply Current	3.6			0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current	3.6			5	mA	Outputs LOW
ΔI_{CC}	Increase in Power Supply Current (Note 6)	3.6			0.2	mA	One Input at V_{CC} − 0.6V Other Inputs at V_{CC} or GND

DC Electrical Characteristics (Continued)

Note 3: All typical values are at V_{CC} = 3.3V, T_A = 25°C.

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			Units	Conditions C_L = 50 pF, R_L = 500Ω
			Min	Typ	Max		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	T_A = −40°C to +85°C, C_L = 50 pF, R_L = 500Ω					Units
		V_{CC} = 3.3V ± 0.3V			V_{CC} = 2.7V		
		Min	Typ (Note 9)	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150			150		MHz
t_{PLH}	Propagation Delay	1.7		4.9	1.7	5.5	ns
t_{PHL}	CP to O_n	1.9		4.8	1.9	5.1	
t_{PHL}	Propagation Delay $\overline{CLR}$ to O_n	1.6		4.8	1.6	5.4	ns
t_W	Pulse Duration	3.3			3.3		ns
t_S	Setup Time Data HIGH or LOW before CP	2.3			2.7		ns
	$\overline{CLR}$ HIGH before CP	2.3			2.7		
t_H	Hold Time Data HIGH or LOW after CP	0			0		ns

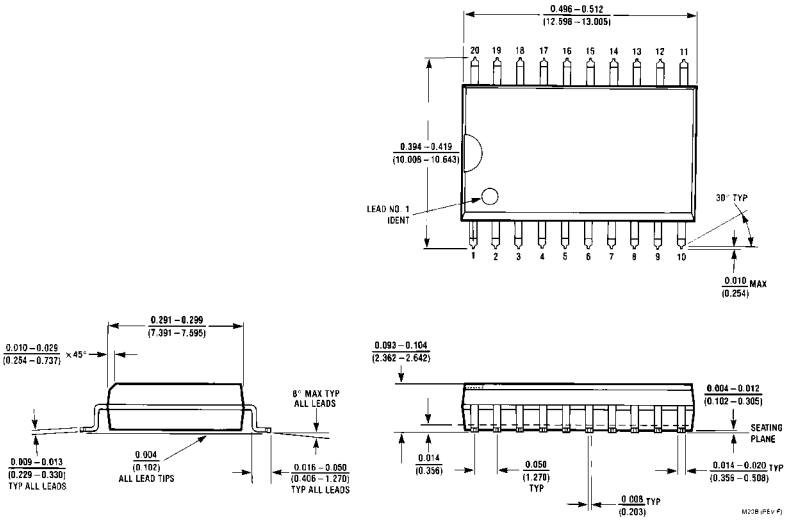
Note 9: All typical values are at V_{CC} = 3.3V, T_A = 25°C.

Capacitance (Note 10)

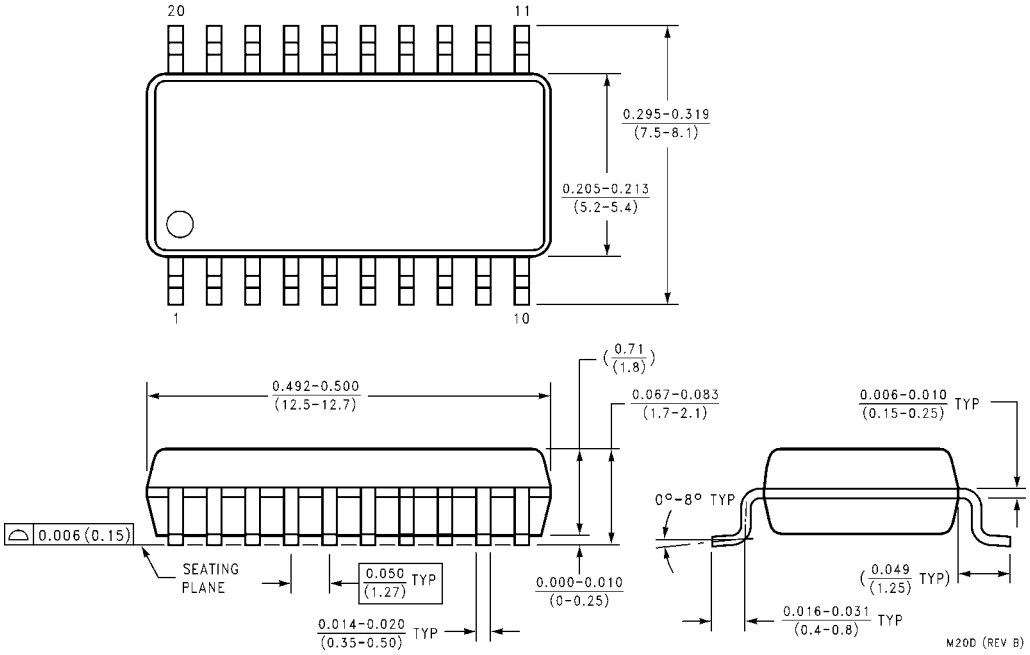
Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = 0V, V_I = 0V or V_{CC}	3	pF
C_{OUT}	Output Capacitance	V_{CC} = 3.0V, V_O = 0V or V_{CC}	6	pF

Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted

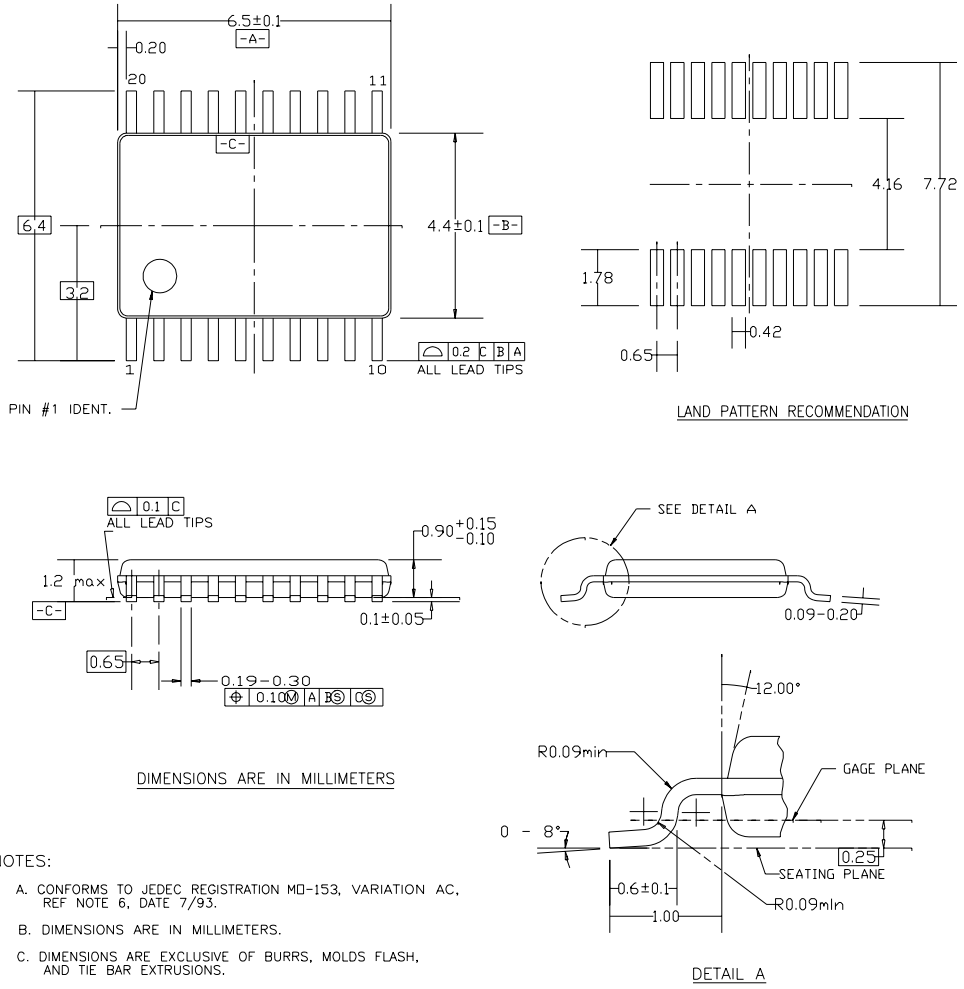


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

FAIRCHILD SEMICONDUCTOR™

November 1999
Revised November 1999

74LVTH543
Low Voltage Octal Registered Transceiver with 3-STATE Outputs (Preliminary)

General Description

The LVTH543 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow.

The LVTH543 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

This octal registered transceiver is designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH543 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

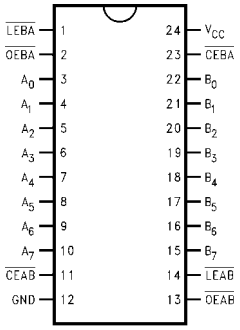
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 543
- Latch-up performance exceeds 500 mA

Ordering Code:

Order Number	Package Number	Package Description
74LVTH543WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH543MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs
$\overline{LEAB}$, $\overline{LEBA}$	Latch Enable Inputs
$\overline{CEAB}$, $\overline{CEBA}$	Chip Enable Inputs
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Functional Description

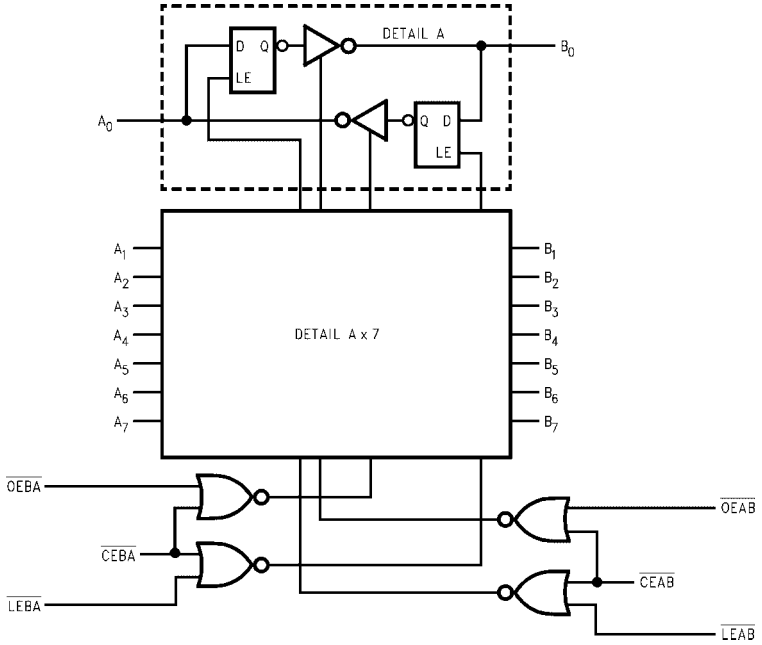
The LVTH543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable ($\overline{CEAB}$) input must be LOW in order to enter data from the A Port or take data from the B Port as indicated in the Data I/O Control Table. With $\overline{CEAB}$ LOW, a low signal on ($\overline{LEAB}$) input makes the A to B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{LEAB}$ line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With $\overline{CEAB}$ and $\overline{OEAB}$ both LOW, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the $\overline{CEBA}$, $\overline{LEBA}$ and $\overline{OEBA}$.

Data I/O Control Table

Inputs			Latch Status	Output Buffers
$\overline{CEAB}$	$\overline{LEAB}$	$\overline{OEAB}$		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$		Units	Conditions
				Min	Max		
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 µA
			2.7	2.4		V	I_{OH} = −8 mA
			3.0	2.0		V	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5	V	I_{OL} = 24 mA
			3.0		0.4	V	I_{OL} = 16 mA
			3.0		0.5	V	I_{OL} = 32 mA
			3.0		0.55	V	I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
				−75		µA	V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive		3.0	500		µA	(Note 3)
	Current to Change State			−500		µA	(Note 4)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6		−5	µA	V_I = 0V
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	0V ≤ V_I or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE		0–1.5V		±100	µA	V_O = 0.5V to 3.0V
	Output Current						V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.6V
$I_{OZH}+$	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$
							Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current		3.6		0.2	mA	One Input at V_{CC} − 0.6V
	(Note 5)						Other Inputs at V_{CC} or GND

Note 3: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 4: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 5: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 6)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			Units	Conditions
			Min	Typ	Max		C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 7)

Note 6: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 7: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

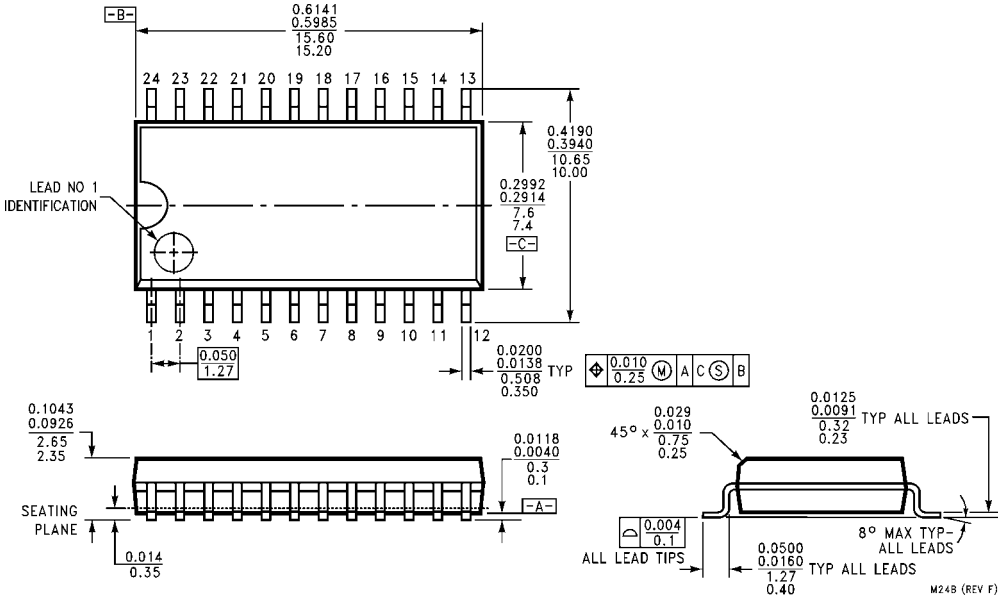
Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
			$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
t_{PLH}	Propagation Delay		1.3	3.7	1.3	4.3	ns
t_{PHL}	Data to Outputs		1.3	3.7	1.3	4.3	
t_{PLH}	Propagation Delay		1.3	4.7	1.3	5.9	ns
t_{PHL}	$\overline{LE}$ to A or B		1.3	4.7	1.3	5.9	
t_{PZH}	Output Enable Time		1.1	4.9	1.1	6.2	ns
t_{PZL}	$\overline{OE}$ to A or B		1.1	4.9	1.1	6.2	
t_{PHZ}	Output Disable Time		2.0	5.3	2.0	5.9	ns
t_{PLZ}	$\overline{OE}$ to A or B		2.0	5.3	2.0	5.9	
t_{PZH}	Output Enable Time		1.3	5.3	1.3	6.8	ns
t_{PZL}	$\overline{CE}$ to A or B		1.3	5.3	1.3	6.8	
t_{PHZ}	Output Disable Time		2.3	5.4	2.3	5.9	ns
t_{PLZ}	$\overline{CE}$ to A or B		2.3	5.4	2.3	5.6	
t_W	Pulse Duration	$\overline{LE}$ LOW	3.3		3.3		ns
t_S	Setup Time	A or B before $\overline{LE}$, Data HIGH	0.4		0.4		ns
		A or B before $\overline{LE}$, Data LOW	1.0		1.5		
		A or B before $\overline{CE}$, Data HIGH	0.2		0.2		
		A or B before $\overline{CE}$, Data LOW	0.7		1.2		
t_H	Hold Time	A or B before $\overline{LE}$, Data HIGH	1.5		0.6		ns
		A or B before $\overline{LE}$, Data LOW	1.3		1.5		
		A or B before $\overline{CE}$, Data HIGH	1.6		0.5		
		A or B before $\overline{CE}$, Data LOW	1.4		1.6		

Capacitance (Note 8)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

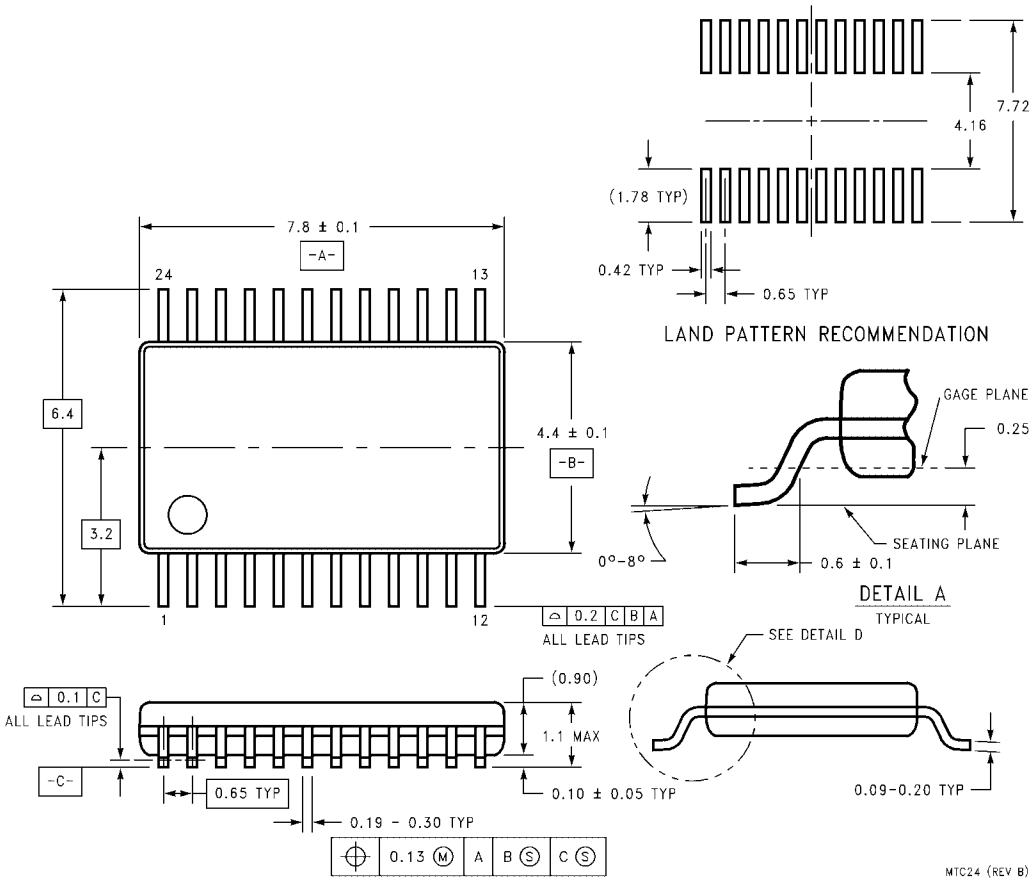
Note 8: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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FAIRCHILD SEMICONDUCTOR™

November 1999
Revised December 1999

74LVTH646
Low Voltage Octal Transceiver/Register with 3-STATE Outputs

General Description

The LVTH646 consists of registered bus transceiver circuits, D-type flip-flops, and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW-to-HIGH transition of the appropriate clock pin (CPAB or CPBA). (See Functional Description)

The LVTH646 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

The bus transceivers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH646 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

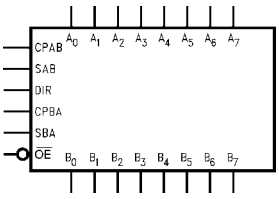
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 646
- Latch-up performance exceeds 500 mA

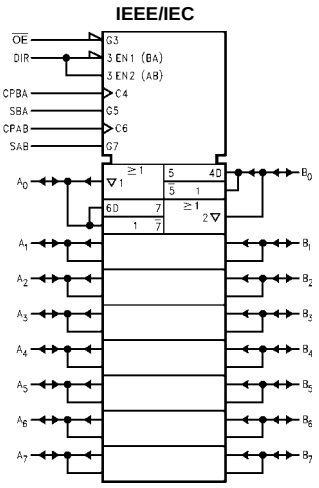
Ordering Code:

Order Number	Package Number	Package Description
74LVTH646WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH646MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

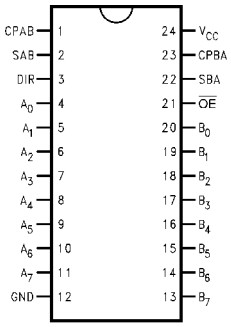
Devices also available in Tape and Reel. Specify by appending letter suffix "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_7	Data Register A Inputs
	Data Register A Outputs
B_0–B_7	Data Register B Inputs
	Data Register B Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
$\overline{OE}$	Output Enable Input
DIR	Direction Control Input

Truth Table

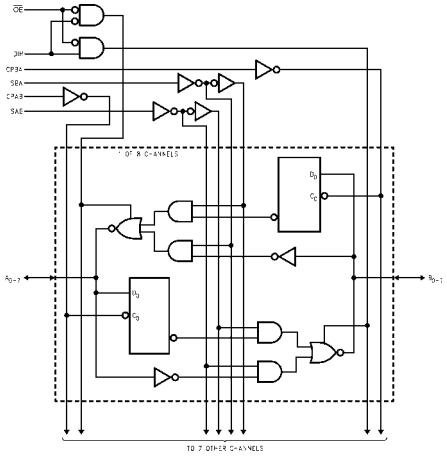
(Note 1)

Inputs						Data I/O		Function
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X			Isolation
H	X	↑	X	X	X	Input	Input	Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X			A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X	Input	Output	Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L			B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L	Output	Input	Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial ↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs.

Logic Diagram



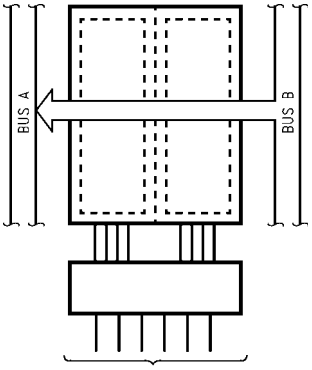
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both. The select (SAB, SBA) controls can multiplex stored and real-time. The examples below demonstrate the four fundamental bus-management functions that can be performed.

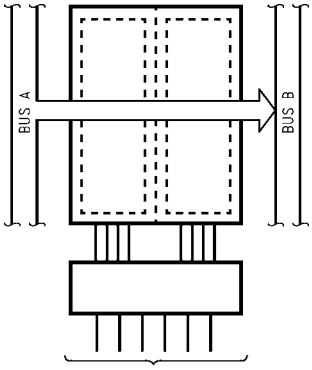
The direction control (DIR) determines which bus will receive data when $\overline{OE}$ is LOW. In the isolation mode ($\overline{OE}$ HIGH), A data may be stored in one register and/or B data may be stored in the other register. When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two busses, A or B, may be driven at a time.

Real-Time Transfer
Bus B to Bus A



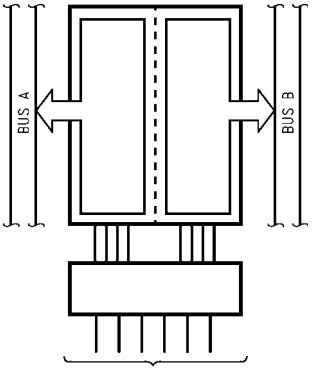
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Real-Time Transfer
Bus B to Bus A



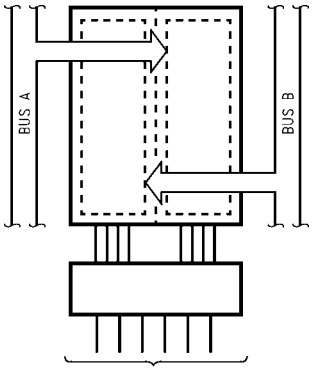
$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	X	X	L	X

Transfer Storage
Data to A or B



$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	L	X	H or L	X	H
L	H	H or L	X	H	X

Storage



$\overline{OE}$	DIR	CPAB	CPBA	SAB	SBA
L	H	↑	X	L	X
L	L	X	↑	X	L
H	X	↑	X	X	X
H	X	X	↑	X	X

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 3)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 3: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C Min	T_A = −40°C to +85°C Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8	V	$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 µA
			2.7	2.4		V	I_{OH} = −8 mA
			3.0	2.0		V	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5	V	I_{OL} = 24 mA
			3.0		0.4	V	I_{OL} = 16 mA
			3.0		0.5	V	I_{OL} = 32 mA
			3.0		0.55	V	I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
				−75		µA	V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive		3.0	500		µA	(Note 4)
	Current to Change State			−500		µA	(Note 5)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6		−5	µA	V_I = 0V
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power Off Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power up/down 3-STATE		0–1.5V		±100	µA	V_O = 0.5V to 3.0V
	Output Current						V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.6V
I_{OZH}+	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
I_{CCZ}+	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$
							Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current		3.6		0.2	mA	One Input at V_{CC} − 0.6V
	(Note 6)						Other Inputs at V_{CC} or GND

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C Min	T_A = 25°C Typ	T_A = 25°C Max	Units	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
			$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		150		150		MHz
t_{PLH}	Propagation Delay Data to Output		1.8	5.7	1.8	6.3	ns
t_{PHL}	Clock to A or B		1.8	5.0	1.8	5.6	
t_{PLH}	Propagation Delay Data to Output		1.3	4.6	1.3	5.0	ns
t_{PHL}	Data to A or B		1.3	4.6	1.3	5.3	
t_{PLH}	Propagation Delay Data to Output		1.5	5.5	1.5	6.5	ns
t_{PHL}	SBA or SAB to A or B		1.5	5.5	1.5	6.3	
t_{PZH}	Output Enable Time		1.1	5.7	1.1	6.8	ns
t_{PZL}	$\overline{OE}$ to A or B		1.1	6.3	1.1	7.3	
t_{PHZ}	Output Disable Time		1.9	5.7	2.3	6.1	ns
t_{PLZ}	$\overline{OE}$ to A or B		1.6	5.5	2.3	5.9	
t_{PZH}	Output Enable Time		1.3	6.1	1.3	6.7	ns
t_{PZL}	DIR to A or B		1.3	6.7	1.3	7.7	
t_{PHZ}	Output Disable Time		1.5	6.2	1.5	7.1	ns
t_{PLZ}	DIR to A or B		1.5	5.6	1.5	6.3	
t_W	Pulse Duration	Clock HIGH or LOW	3.3		3.3		ns
t_S	Setup Time	A or B Before Clock, Data HIGH	1.2		1.5		ns
		A or B Before Clock, Data LOW	1.6		2.2		
t_H	Hold Time	A or B after Clock	0.8		0.8		ns
t_{OSHL}	Output to Output Skew (Note 9)			1.0		1.0	ns
t_{OSLH}				1.0		1.0	

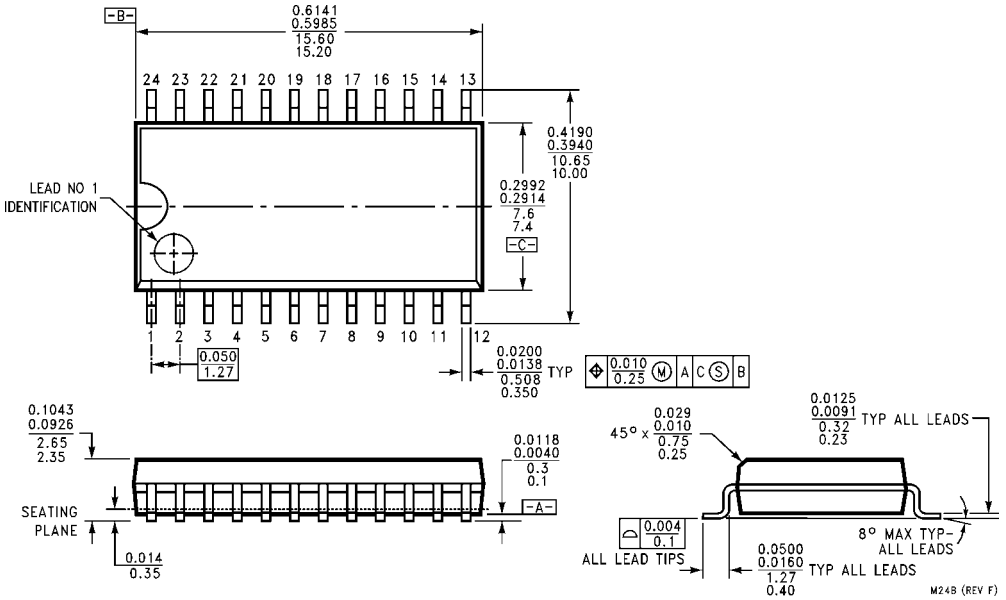
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 10)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

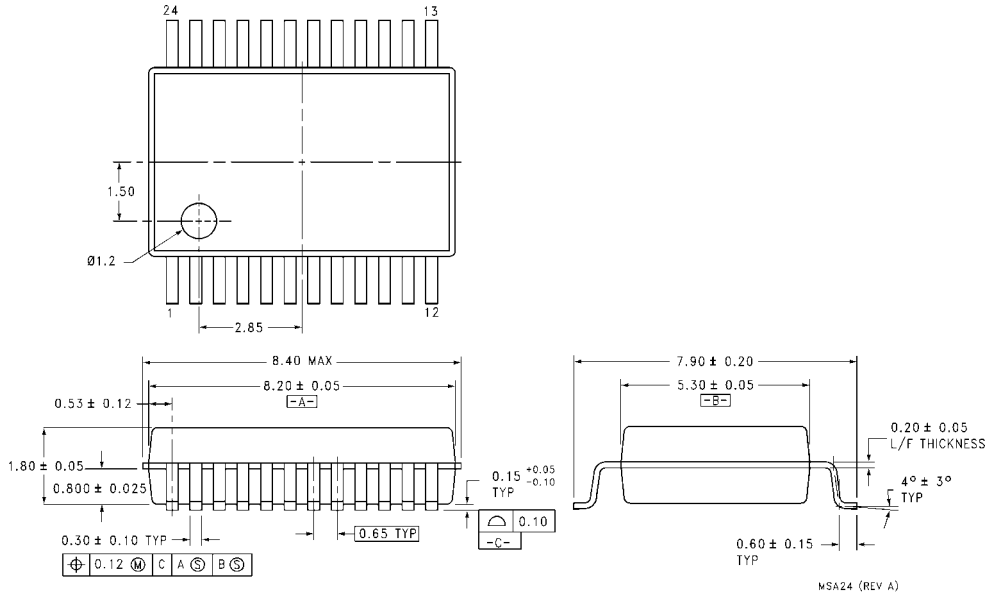
Note 10: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MSA24

FAIRCHILD SEMICONDUCTOR™

November 1999
Revised November 1999

74LVTH652
Low Voltage Octal Transceiver/Register with 3-STATE Outputs (Preliminary)

General Description

The LVTH652 consists of bus transceiver circuits with D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, $\overline{\text{OEBA}}$) are provided to control the transceiver function. (See Functional Description).

The LVTH652 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

This bus/octal buffer and line driver is designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH652 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

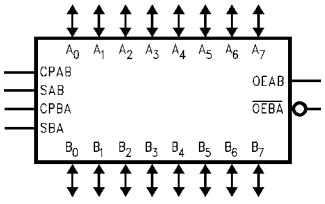
- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –32 mA/+64 mA
- Functionally compatible with the 74 series 652
- Latch-up performance exceeds 500 mA

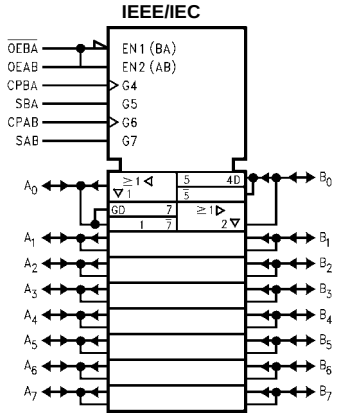
Ordering Code:

Order Number	Package Number	Package Description
74LVTH652WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide
74LVTH652MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

Logic Symbols

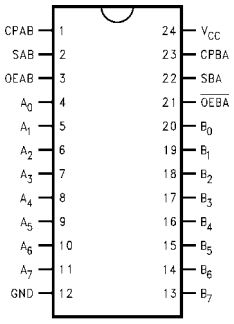




Pin Descriptions

Pin Names	Description
A_0–A_7	Data Register A Inputs/ 3-STATE Outputs
B_0–B_7	Data Register B Inputs/ 3-STATE Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{OEBA}$	Output Enable Inputs

Connection Diagram



Truth Table

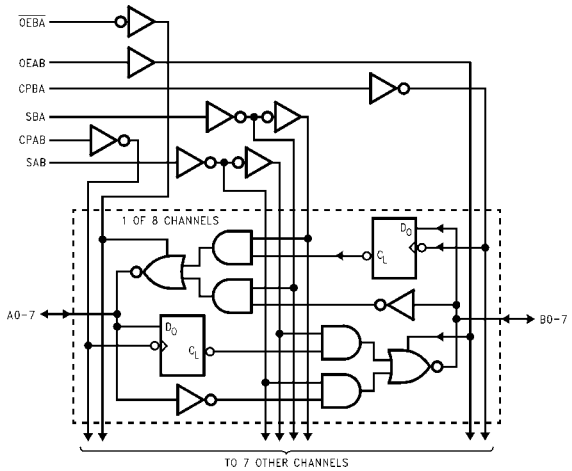
(Note 1)

Inputs						Inputs/Outputs		Operating Mode
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	A_0 thru A_7	B_0 thru B_7	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	N	N	X	X			Store A and B Data
X	H	N	H or L	X	X	Input	Not Specified	Store A, Hold B
H	H	N	N	X	X	Input	Output	Store A in Both Registers
L	X	H or L	N	X	X	Not Specified	Input	Hold A, Store B
L	L	N	N	X	X	Output	Input	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Store B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial N = LOW to HIGH Clock Transition

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or $\overline{OEBA}$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

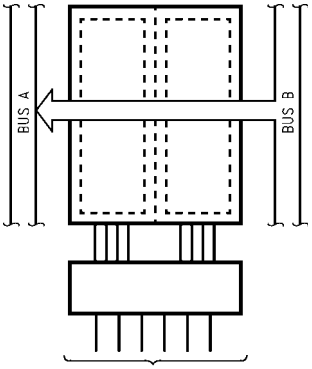
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples below demonstrate the four fundamental bus-management functions that can be performed with the LVTH652.

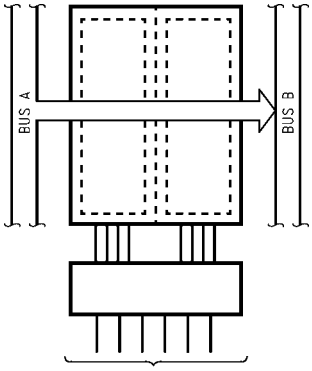
Data on the A or B data bus, or both can be stored in the internal D-type flip-flop by LOW-to-HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and $\overline{\text{OEBA}}$. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Real-Time Transfer
Bus B to Bus A



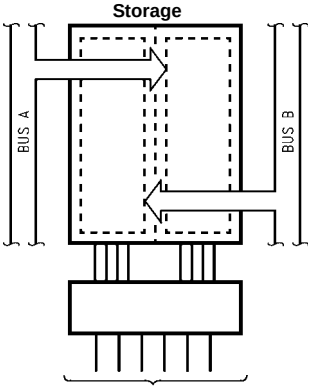
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
L	L	X	X	X	L

Real-Time Transfer
Bus A to Bus B



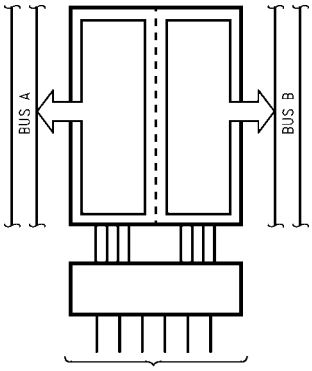
OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	H	X	X	L	X

Storage



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
X	H	N	X	X	X
L	X	X	N	X	X
L	H	N	N	X	X

Transfer Storage
Data to A or B



OEAB	$\overline{\text{OEBA}}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 3)	
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V	0	10	ns/V

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 3: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$ Min	$T_A = -40°C$ to $+85°C$ Max	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		2.7		−1.2	V	I_I = −18 mA
V_{IH}	Input HIGH Voltage		2.7–3.6	2.0		V	$V_O \le 0.1V$ or
V_{IL}	Input LOW Voltage		2.7–3.6		0.8		$V_O \ge V_{CC} - 0.1V$
V_{OH}	Output HIGH Voltage		2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 µA
			2.7	2.4		V	I_{OH} = −8 mA
			3.0	2.0		V	I_{OH} = −32 mA
V_{OL}	Output LOW Voltage		2.7		0.2	V	I_{OL} = 100 µA
			2.7		0.5	V	I_{OL} = 24 mA
			3.0		0.4	V	I_{OL} = 16 mA
			3.0		0.5	V	I_{OL} = 32 mA
			3.0		0.55	V	I_{OL} = 64 mA
$I_{I(HOLD)}$	Bushold Input Minimum Drive		3.0	75		µA	V_I = 0.8V
				−75		µA	V_I = 2.0V
$I_{I(OD)}$	Bushold Input Over-Drive		3.0	500		µA	(Note 4)
	Current to Change State			−500		µA	(Note 5)
I_I	Input Current		3.6		10	µA	V_I = 5.5V
		Control Pins	3.6		±1	µA	V_I = 0V or V_{CC}
		Data Pins	3.6		−5	µA	V_I = 0V
					1	µA	$V_I = V_{CC}$
I_{OFF}	Power OFF Leakage Current		0		±100	µA	$0V \le V_I$ or $V_O \le 5.5V$
$I_{PU/PD}$	Power Up/Down 3-STATE		0–1.5V		±100	µA	V_O = 0.5V to 3.0V
	Output Current						V_I = GND or V_{CC}
I_{OZL}	3-STATE Output Leakage Current		3.6		−5	µA	V_O = 0.0V
I_{OZH}	3-STATE Output Leakage Current		3.6		5	µA	V_O = 3.6V
$I_{OZH}+$	3-STATE Output Leakage Current		3.6		10	µA	$V_{CC} < V_O \le 5.5V$
I_{CCH}	Power Supply Current		3.6		0.19	mA	Outputs HIGH
I_{CCL}	Power Supply Current		3.6		5	mA	Outputs LOW
I_{CCZ}	Power Supply Current		3.6		0.19	mA	Outputs Disabled
$I_{CCZ}+$	Power Supply Current		3.6		0.19	mA	$V_{CC} \le V_O \le 5.5V$
							Outputs Disabled
ΔI_{CC}	Increase in Power Supply Current		3.6		0.2	mA	One Input at V_{CC} − 0.6V
	(Note 6)						Other Inputs at V_{CC} or GND

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Min	$T_A = 25°C$ Typ	$T_A = 25°C$ Max	Units	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3		0.8		V	(Note 8)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

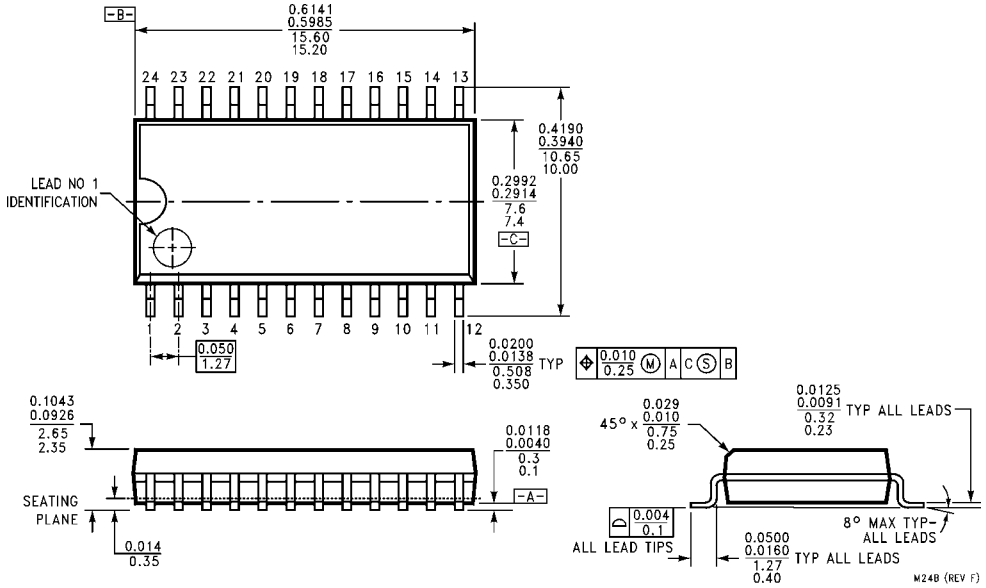
Symbol	Parameter		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $R_L = 500\Omega$				Units
			$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency		150		150		MHz
t_{PLH}	Propagation Delay Data to Output		1.8	4.7	1.8	5.6	ns
t_{PHL}	Clock to A or B		1.8	4.7	1.8	5.6	
t_{PLH}	Propagation Delay Data to Output		1.3	3.5	1.3	4.1	ns
t_{PHL}	Data to A or B		1.3	3.5	1.3	4.1	
t_{PLH}	Propagation Delay Data to Output		1.5	4.9	1.5	6.0	ns
t_{PHL}	SBA or SAB to A or B		1.5	4.9	1.5	6.0	
t_{PZH}	Output Enable Time		1.1	5.2	1.1	6.5	ns
t_{PZL}	$\overline{OE}$ to A or B		1.1	5.2	1.1	6.5	
t_{PHZ}	Output Disable Time		2.3	5.5	2.3	6.1	ns
t_{PLZ}	$\overline{OE}$ to A or B		2.3	5.5	2.3	5.9	
t_{PZH}	Output Enable Time		1.3	4.7	1.3	5.7	ns
t_{PZL}	OE to A or B		1.3	4.7	1.3	5.7	
t_{PHZ}	Output Disable Time		1.5	5.6	1.5	6.7	ns
t_{PLZ}	OE to A or B		1.5	5.6	1.5	6.3	
t_W	Pulse Duration	Clock HIGH or LOW	3.3		3.3		ns
t_S	Setup Time	Data HIGH or LOW before CP	1.2		1.5		ns
		$\overline{CLR}$ HIGH before CP	1.6		2.2		
t_H	Hold Time	Data HIGH or LOW after CP	0.8		0.8		ns

Capacitance (Note 9)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V$, $V_I = 0V$ or V_{CC}	4	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.0V$, $V_O = 0V$ or V_{CC}	8	pF

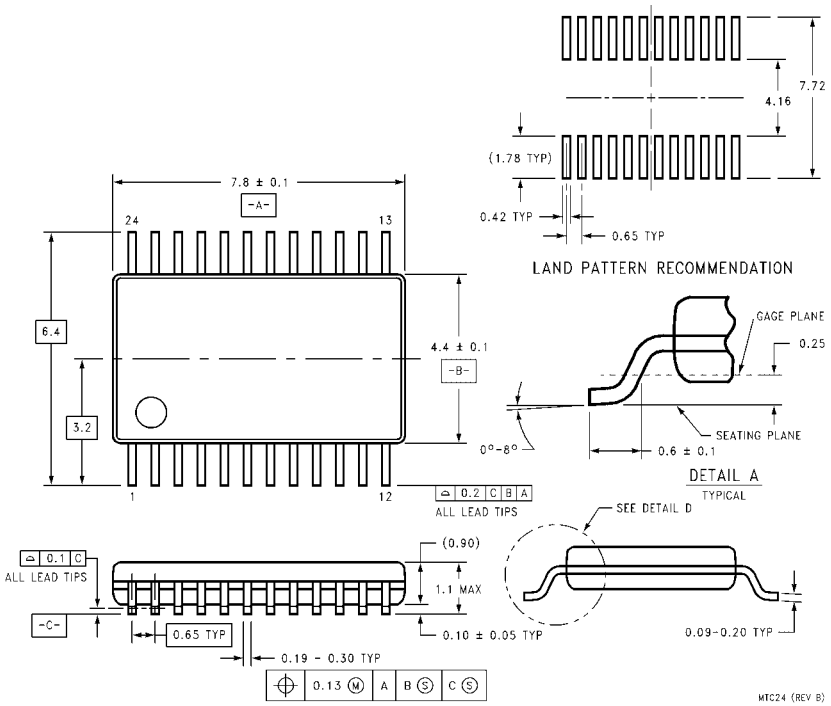
Note 9: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead (0.300' Wide) Molded Small Outline Package, SOIC JEDEC
Package Number M24B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Molded Small Outline Package, TSSOP JEDEC
Package Number MTC24

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1993
Revised March 1999

74LVX00
Low Voltage Quad 2-Input NAND Gate

General Description

The LVX00 contains four 2-input NAND gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

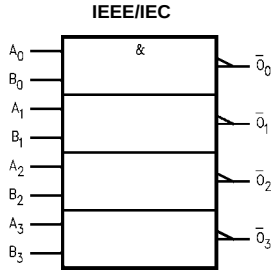
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

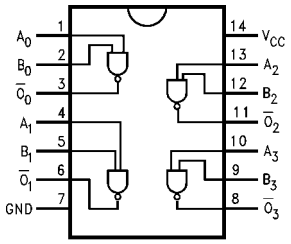
Order Number	Package Number	Package Description
74LVX00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operarting Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input	2.0	1.5			1.5				
	Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level Input	2.0			0.5		0.5			
	Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
	Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
	Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		5.4	10.1	1.0	12.5	ns	15
t_{PHL}				7.9	13.6	1.0	16.0		50
		3.3 ± 0.3		4.1	6.2	1.0	7.5		15
				6.6	9.7	1.0	11.0		50
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	50
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

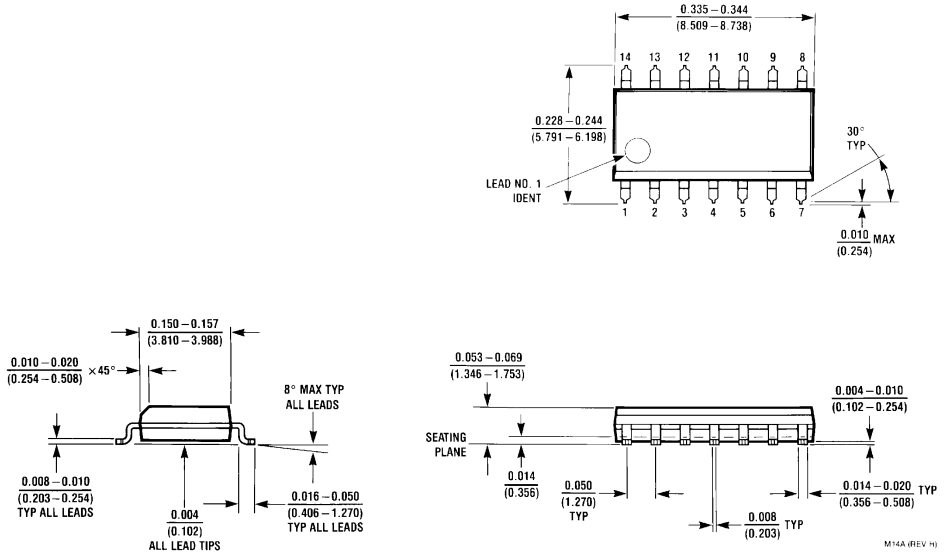
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		19				pF

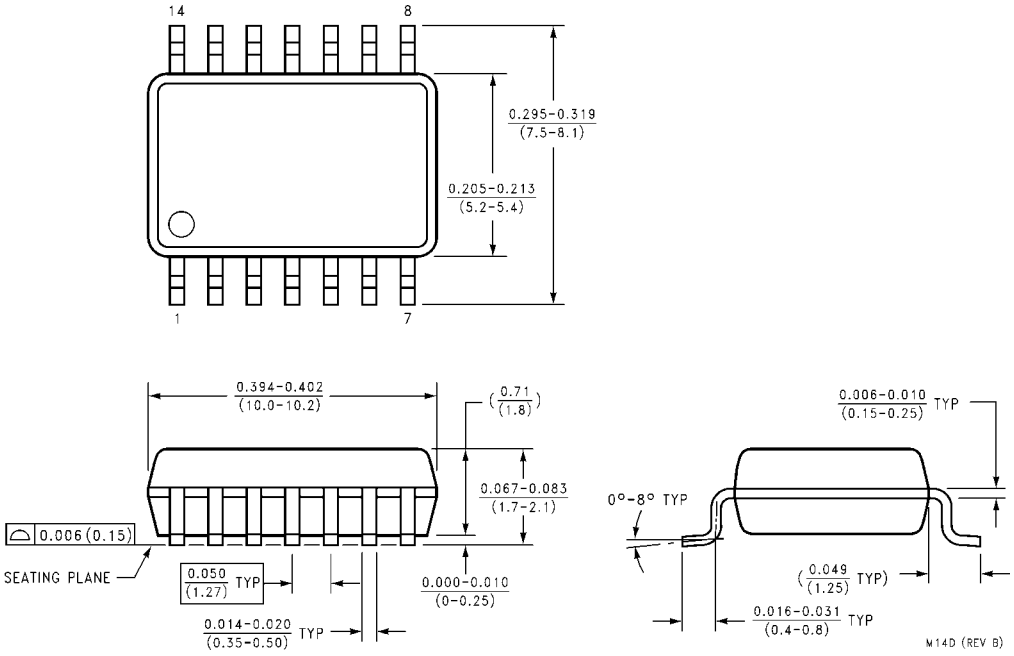
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \dfrac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per Gate)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

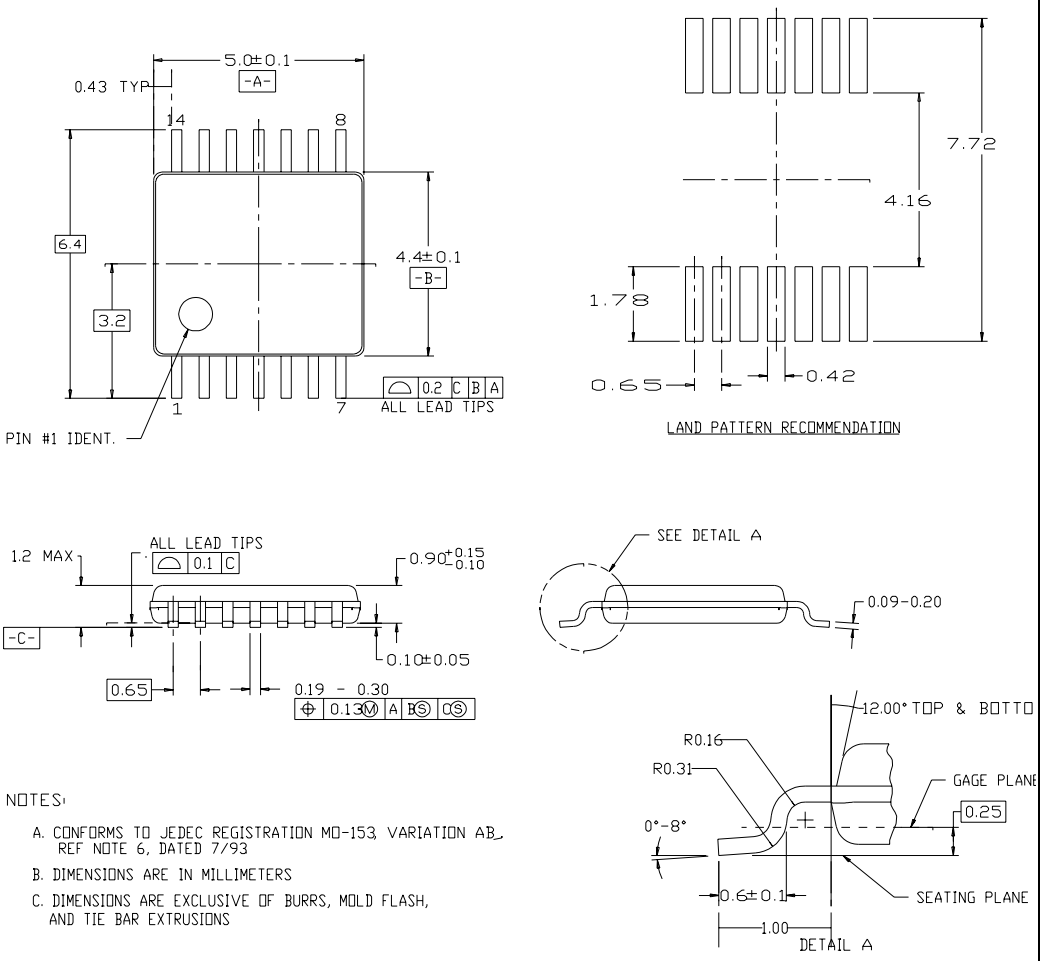


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX02
Low Voltage Quad 2-Input NOR Gate

General Description

The LVX02 contains four 2-input NOR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

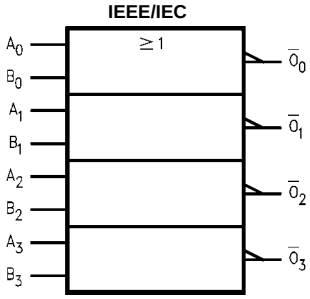
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code

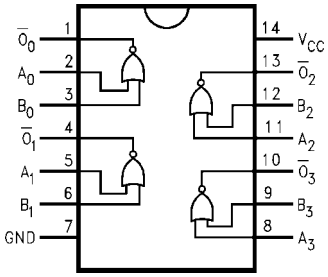
Order Number	Package Number	Package Description
74LVX02M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.5			1.5		V		
		3.0	2.0			2.0				
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5	V		
		3.0			0.8		0.8			
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		5.9	10.7	1.0	13.5	ns	15
t_{PHL}				8.4	14.2	1.0	17.0		50
		3.3 ± 0.3		4.5	6.6	1.0	8.0		15
				7.0	10.1	1.0	11.5		50
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	50
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} t_{PLHm}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLm}|$

Capacitance

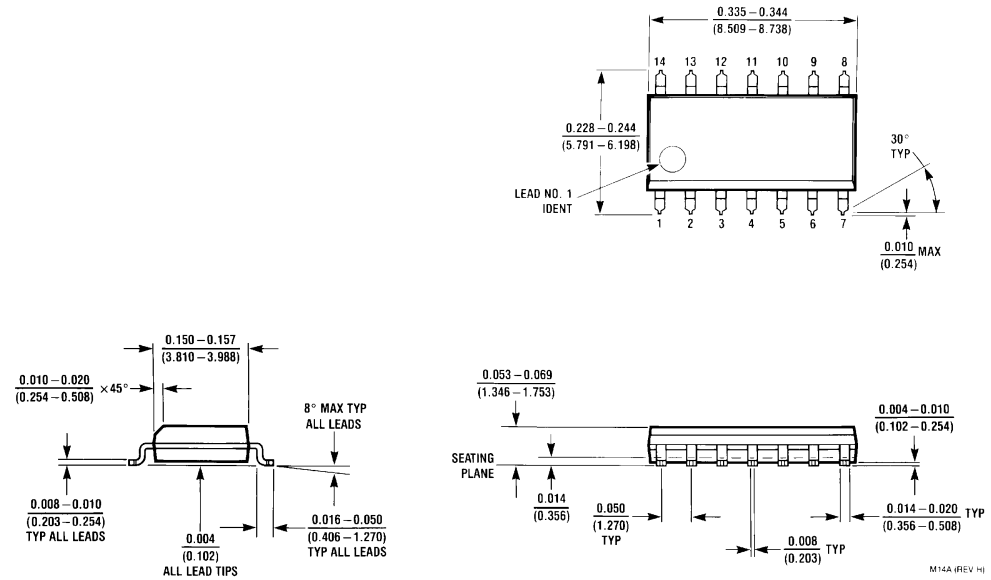
Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		15				pF

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

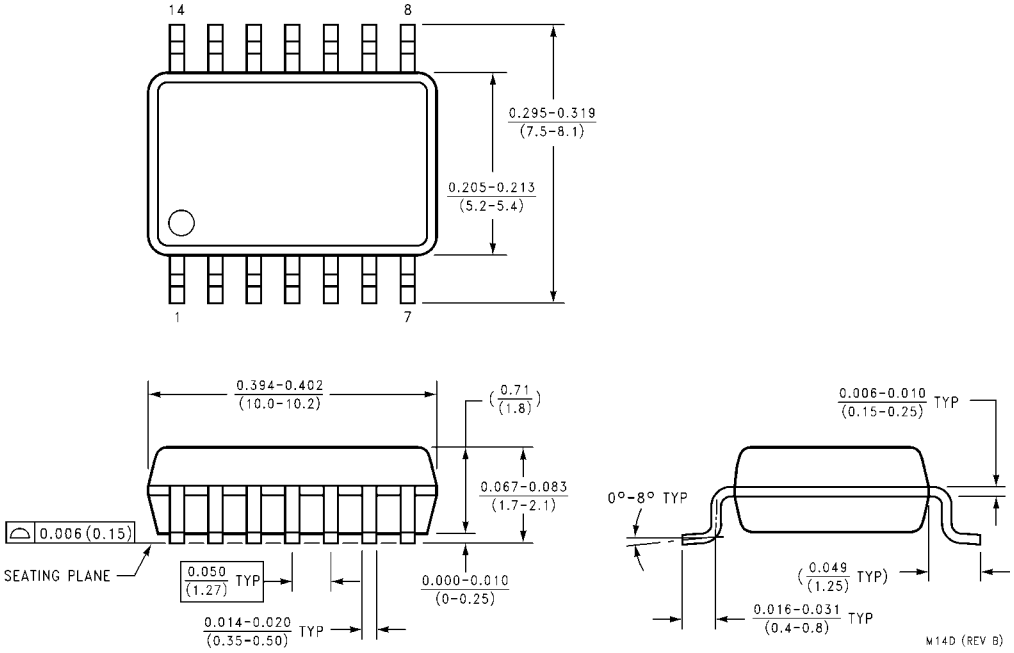
Average operating current can be obtained by the equation:

$$\text{Average operating current can be obtained by the equation: } I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per Gate)}}$$

Physical Dimensions inches (millimeters) unless otherwise noted

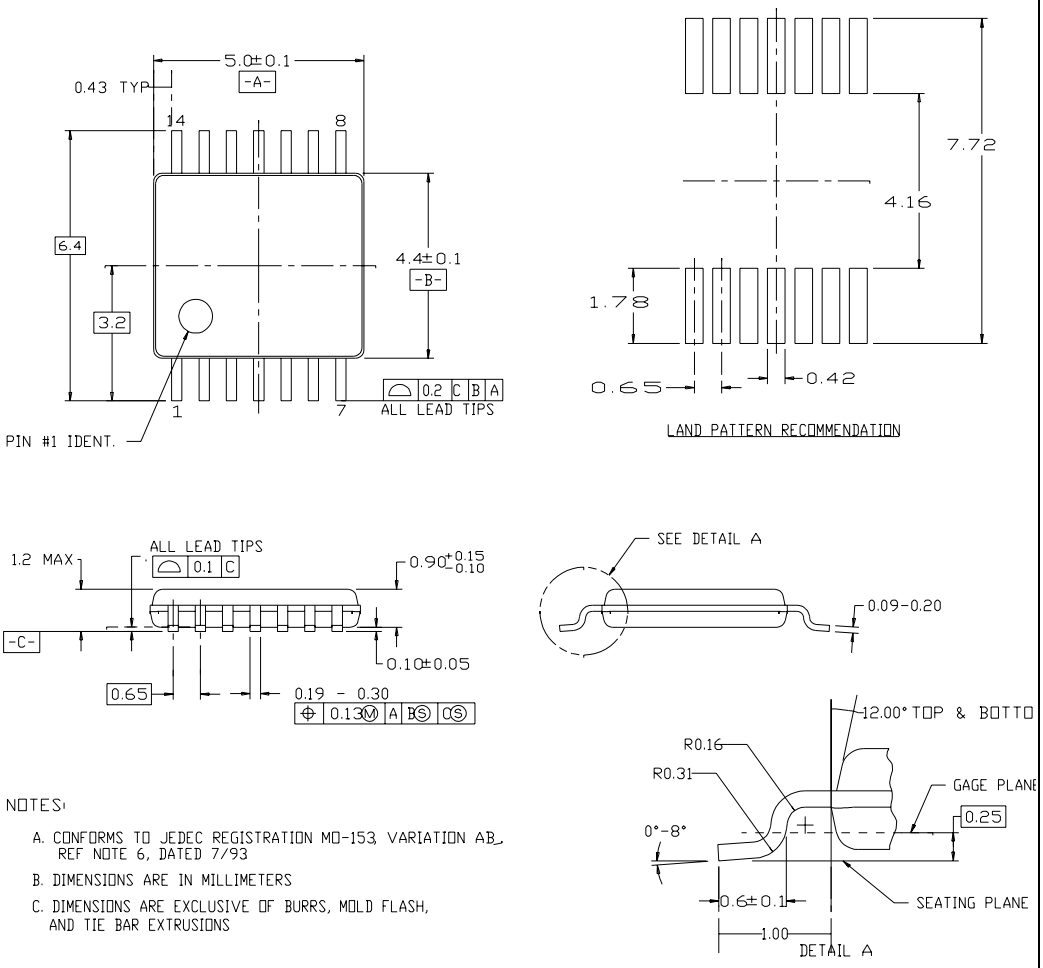


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120A, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX04
Low Voltage Hex Inverter

General Description

The LVX04 contains six inverters. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

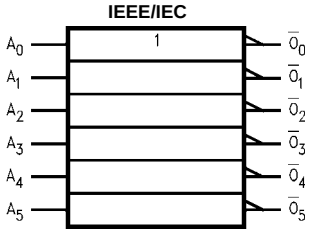
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code

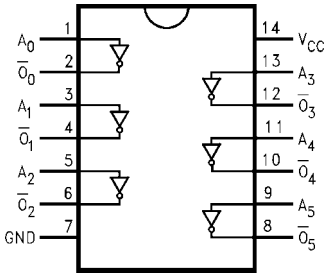
Order Number	Package Number	Package Description
74LVX04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX04MTC	MTC14	14-Lead Thin Shrink Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input	2.0	1.5			1.5				
	Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level Input	2.0			0.5		0.5			
	Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
	Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
	Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		5.4	10.1	1.0	12.5	ns	15
t_{PHL}				7.9	13.6	1.0	16.0		50
		3.3 ± 0.3		4.1	6.2	1.0	7.5		15
				6.6	9.7	1.0	11.0		50
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	50
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.

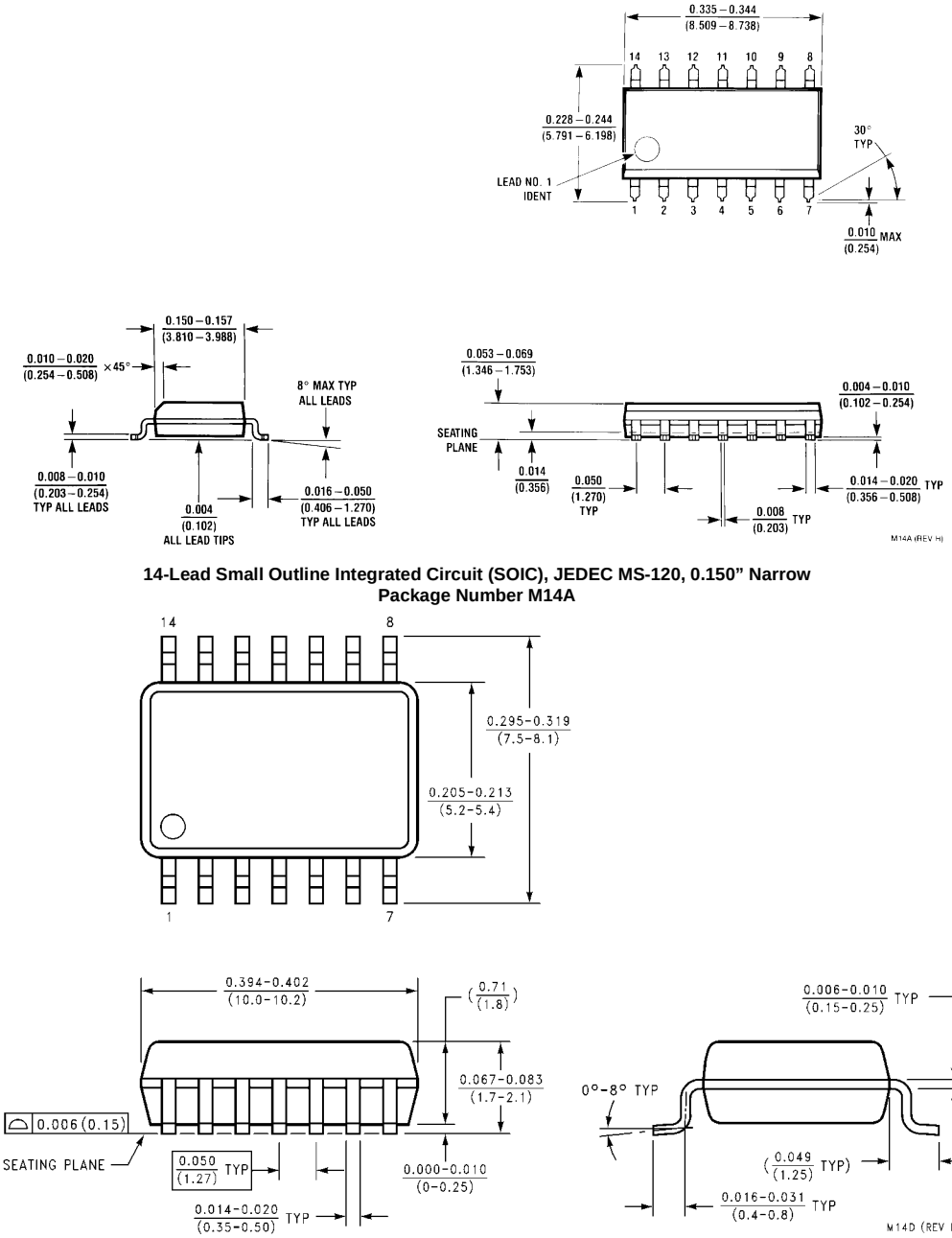
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		18				pF

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{6 \text{ (per Gate)}}$

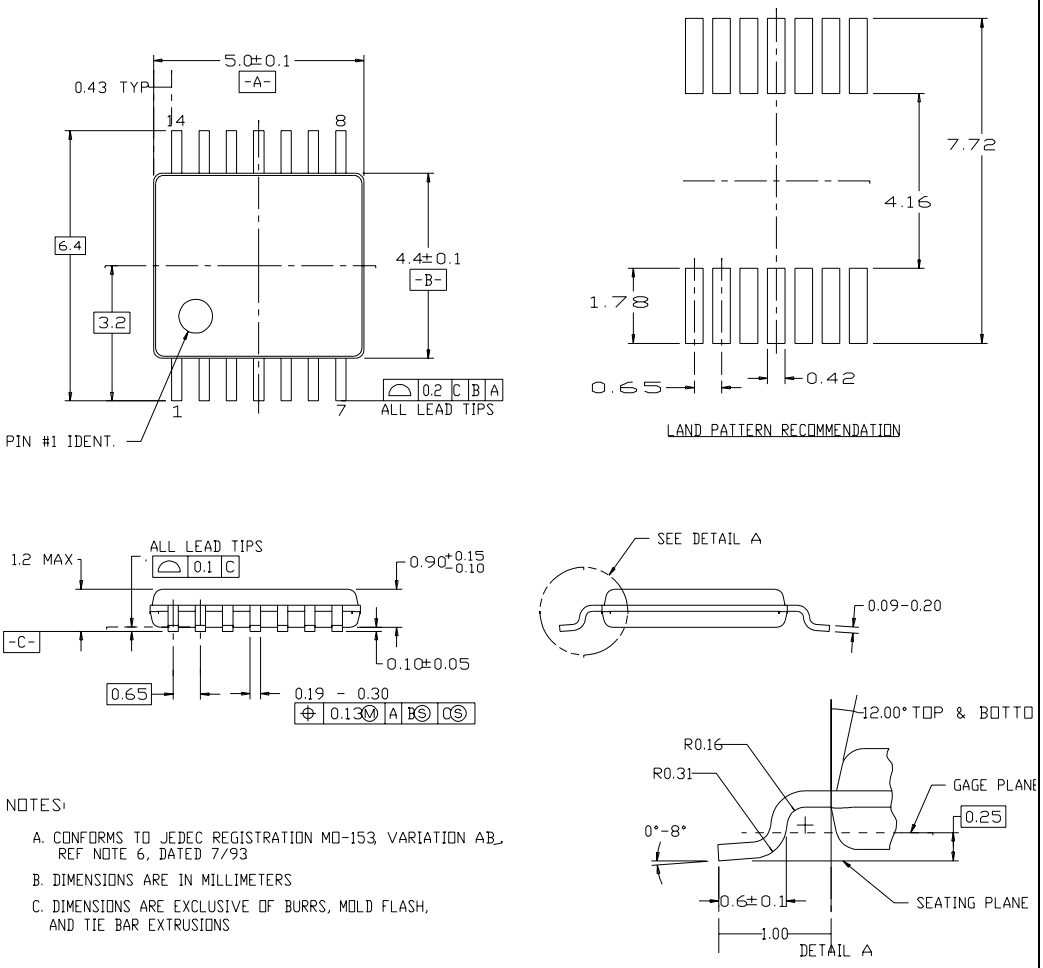
Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX08
Low Voltage Quad 2-Input AND Gate

General Description

The LVX08 contains four 2-input AND gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

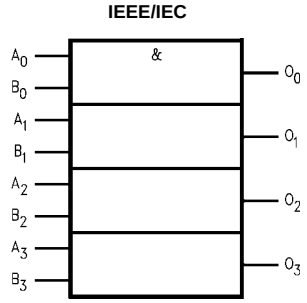
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

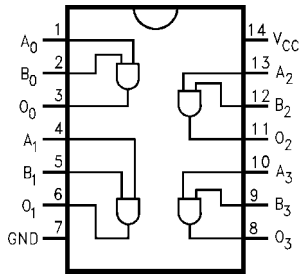
Order Number	Package Number	Package Description
74LVX08M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX08SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW
Lead Temperature (T_L)	
(Soldering, 10 seconds)	240°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1			1.5				
		3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5			
		3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		6.3	11.4	1.0	13.5	ns	15
t_{PHL}				8.8	14.9	1.0	17.0		50
		3.3 ± 0.3		4.8	7.1	1.0	8.5		15
				7.3	10.6	1.0	12.0		50
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	50
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

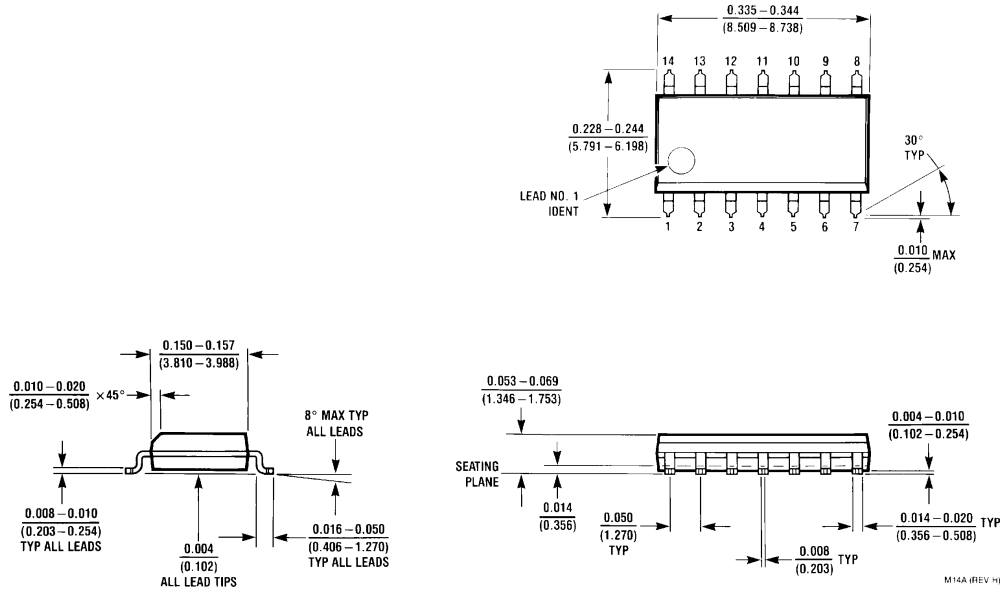
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		18				pF

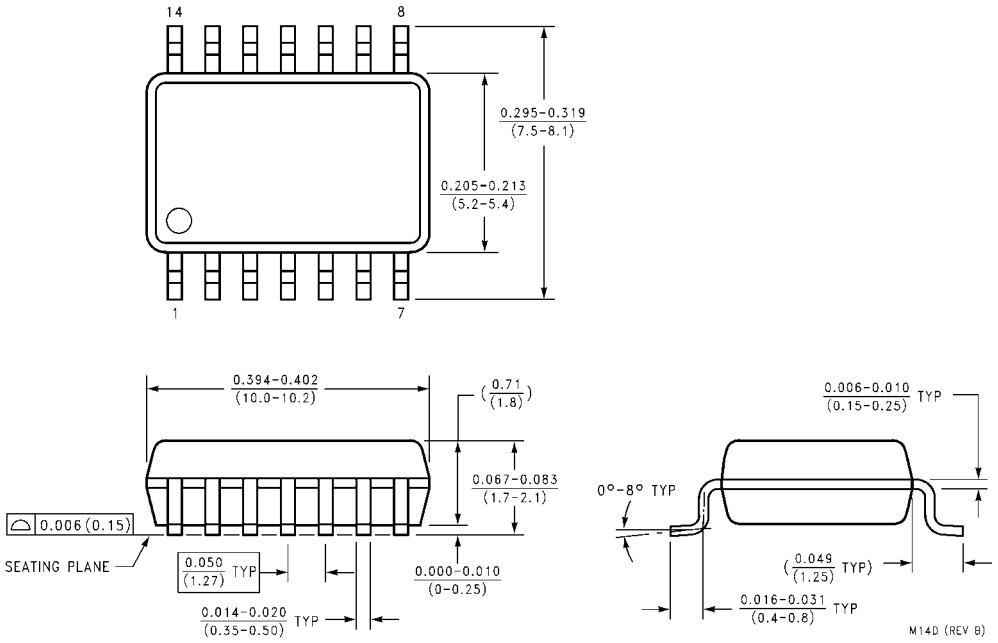
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per Gate)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

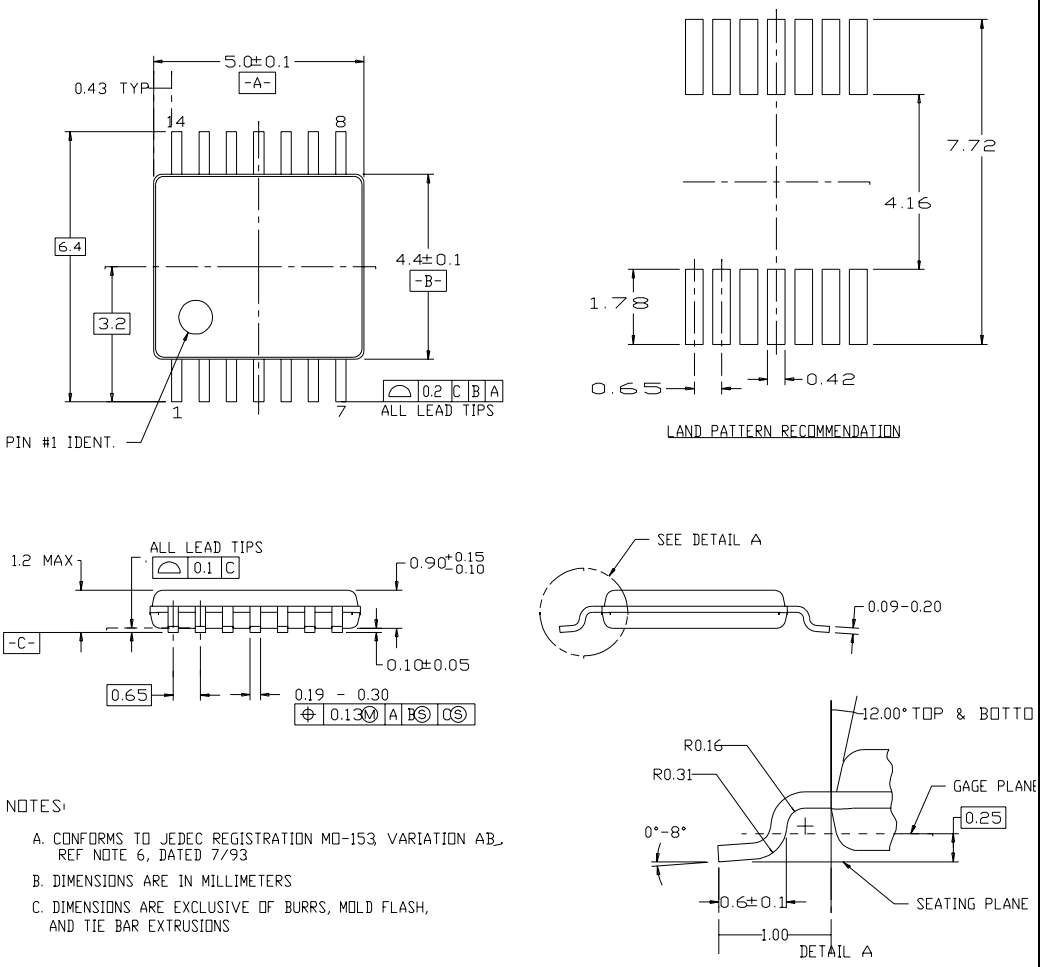


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

October 1996
Revised March 1999

74LVX112
Low Voltage Dual J-K Flip-Flops with Preset and Clear

General Description

The LVX112 is a dual J-K Flip-Flop where each flip-flop has independent inputs (J, K, PRESET, CLEAR, and CLOCK) and outputs (Q, $\overline{Q}$). These devices are edge sensitive and change states synchronously on the negative going transition of the clock pulse. Triggering occurs at a voltage level of the clock and is not directly related to the transition time. Clear and Preset are independent of the clock and are accomplished by a low logic level on the corresponding input. The J and K inputs can change when the clock is in either state without affecting the flip-flop, provided that they are in the desired state during the recommended setup and hold times relative to the falling edge of the clock.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

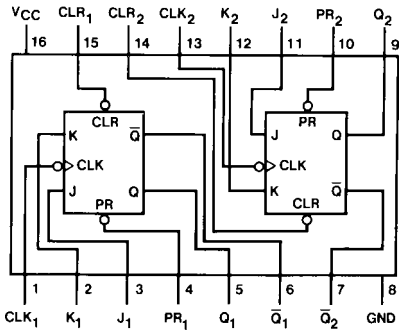
- Input voltage level translation from 5V–3V
- Ideal for low power/low noise 3.3V applications

Ordering Code:

Order Number	Package Number	Package Description
74LVX112M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX112SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX112MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
J_1, J_2, K_1, K_2	Data Inputs
CLK_1, CLK_2	Clock Pulse Inputs (Active Falling edge)
CLR_1, CLR_2	Direct Clear Inputs (Active LOW)
PR_1, PR_2	Direct Preset Inputs (Active LOW)
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	

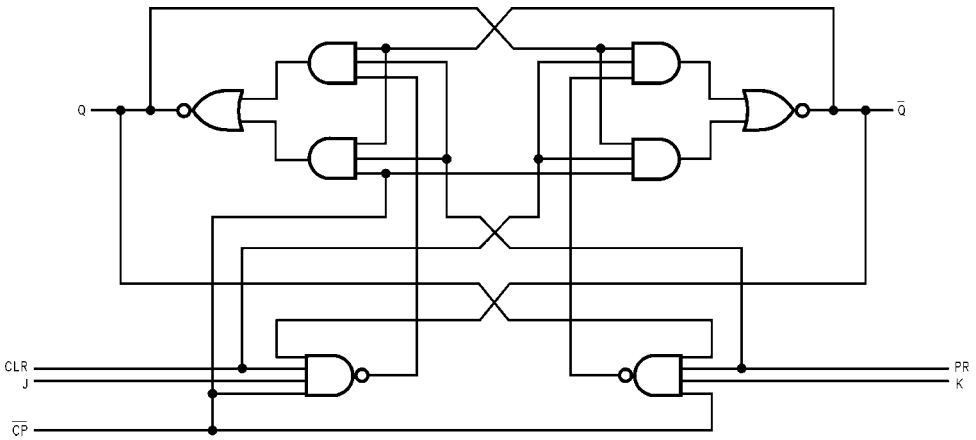
Truth Table

Inputs					Outputs	
PR	CLR	$\overline{CP}$	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	h	h	$\overline{Q}_0$	Q_0
H	H	⌐	l	h	L	H
H	H	⌐	h	l	H	L
H	H	⌐	l	l	Q_0	$\overline{Q}_0$

H (h) = HIGH Voltage Level
L (l) = LOW Voltage Level
X = Immaterial
⌐ = HIGH-to-LOW Clock Transition
Q_0 ($\overline{Q}_0$) = Before HIGH-to-LOW Transition of Clock
Lower case letters indicate the state of the referenced input or output one setup time prior to the HIGH-to-LOW clock transition.

Logic Diagram

(One Half Shown)



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δ_t/Δ_v)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	Low Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	2.7		7.5	12.0	1.0	14.2	ns	15
t_{PHL}	CP_n to Q_n or $\overline{Q}_n$			11.0	16.7	1.0	19.0		50
		3.3 ± 0.3		8.5	11.0	1.0	13.4		15
				10.0	15.0	1.0	16.5		50
t_{PLH}	Propagation Delay	2.7		7.0	11.5	1.0	12.3	ns	15
t_{PHL}	PR or CLR to Q_n or $\overline{Q}_n$			10.1	14.3	1.0	16.5		50
		3.3 ± 0.3		6.7	10.2	1.0	11.7		15
				9.7	13.5	1.0	15.0		50
t_W	Pulse Width	2.7	5.0			5.0		ns	
	(CP or CLR or PR)	3.3 ± 0.3	5.0			5.0			
t_S	Setup Time	2.7	5.5			5.5		ns	
	(J_n or K_n to CP_n)	3.3 ± 0.3	5.0			5.0			
t_H	Hold Time	2.7	1.0			1.0		ns	
	(J_n or K_n to CP_n)	3.3 ± 0.3	1.0			1.0			
t_{REC}	Recovery Time	2.7	6.5			6.5		ns	
	(CLR or PR to CP)	3.3 ± 0.3	6.0			6.0			
f_{MAX}	Maximum Clock	2.7	90	140		85		MHz	15
	Frequency		85	115		70			50
		3.3 ± 0.3	110	150		100			15
			90	120		80			50
t_{OSLH},	Output to Output Skew	2.7			1.5		1.5	ns	50
t_{OSHL}	(Note 3)	3.3			1.5		1.5		

Note 3: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSLH} = |t_{PHLm} - t_{PHLn}|$

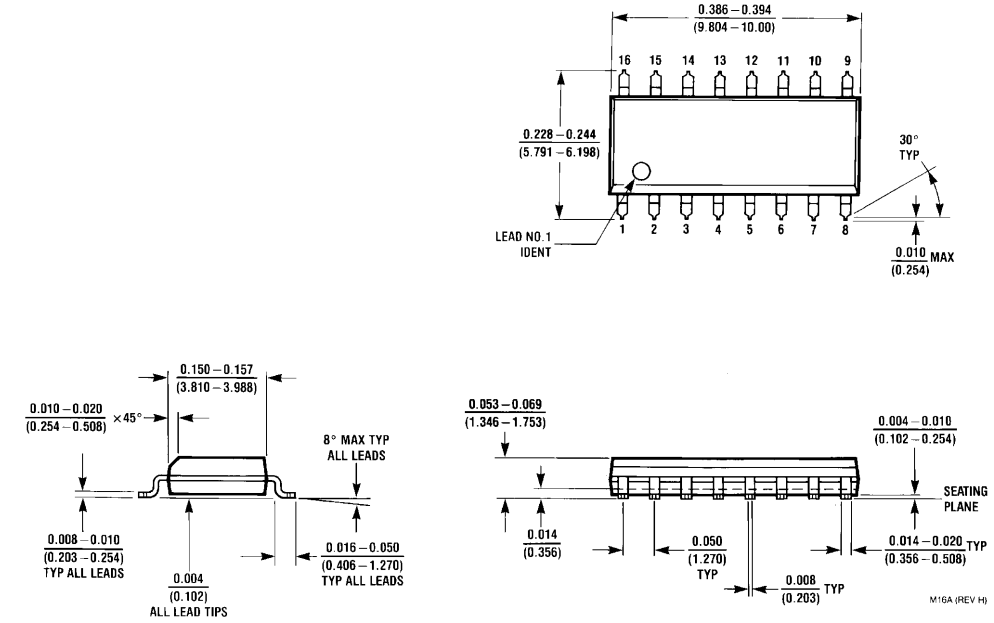
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 4)		18				pF

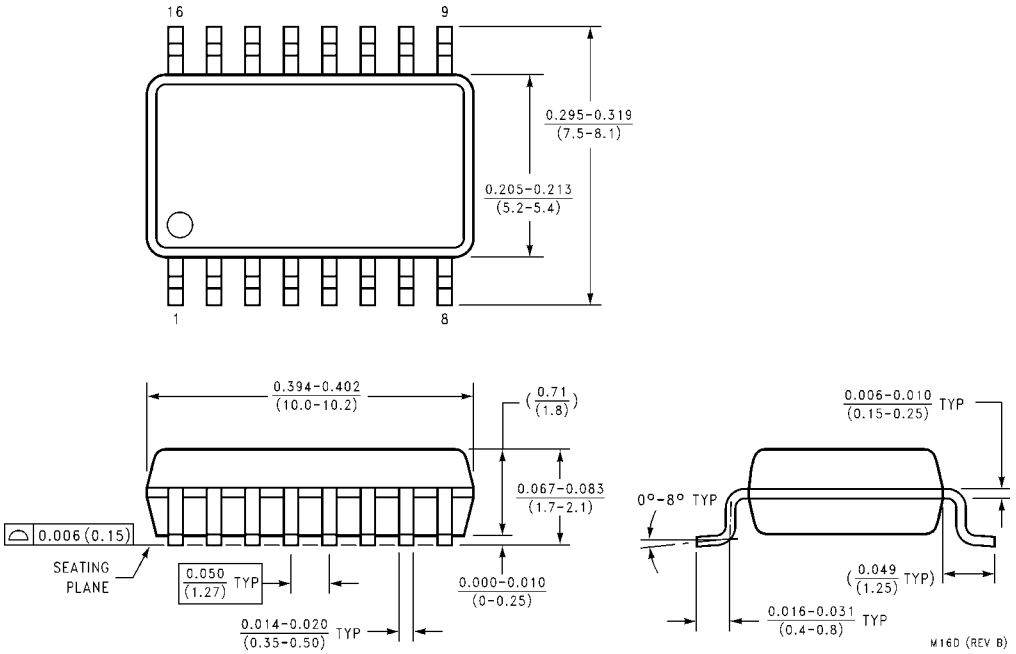
Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \dfrac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{2 \text{ (per F/F)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

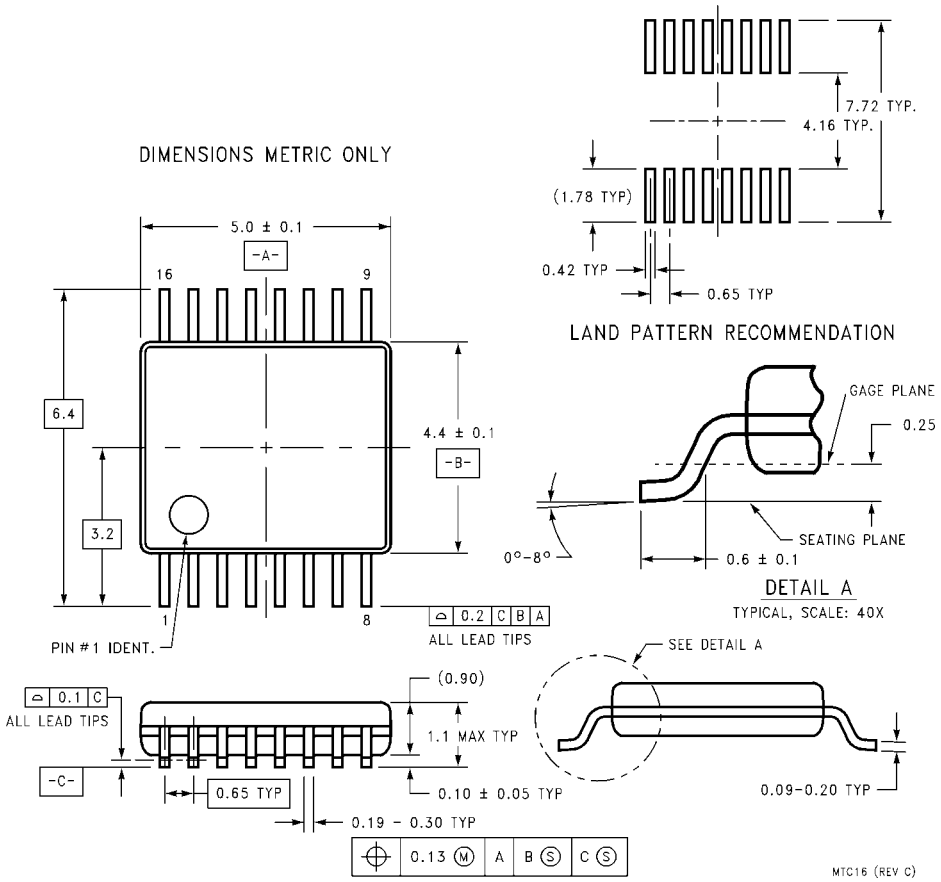


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

FAIRCHILD SEMICONDUCTOR™

February 1994
Revised March 1999

74LVX125
Low Voltage Quad Buffer with 3-STATE Outputs

General Description

The LVX125 contains four independent non-inverting buffers with 3-STATE outputs. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

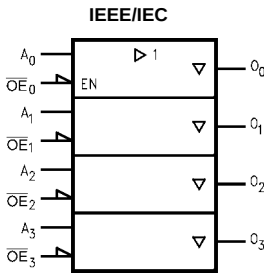
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

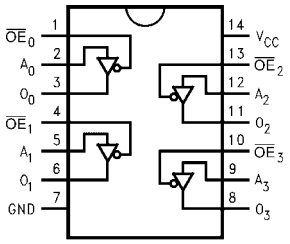
Order Number	Package Number	Package Description
74LVX125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{OE}_n$	Output Enable Inputs
O_n	Outputs

Truth Table

Inputs		Output
$\overline{OE}_n$	A_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK}) V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to +7.0V
DC Output Diode Current (I_{OK})	
V_O = 0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.5			1.5		V		
		3.0	2.0			2.0				
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5	V		
		3.0			0.8		0.8			
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output Off-State Current	3.6			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		5.8	10.1	1.0	13.5	ns	$C_L = 15$ pF
t_{PHL}	Data to Output			8.3	13.6	1.0	17.0		$C_L = 50$ pF
		3.3 ± 0.3		4.4	6.2	1.0	8.5		$C_L = 15$ pF
				6.9	9.7	1.0	12.0		$C_L = 50$ pF
t_{PZH}	Output Enable Time	2.7		5.3	9.3	1.0	12.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZL}				7.8	12.8	1.0	16.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		4.0	5.6	1.0	7.5		$C_L = 15$ pF, $R_L = 1$ kΩ
				6.5	9.1	1.0	11.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Output Disable	2.7		10.0	15.7	1.0	19.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	Time	3.3 ± 0.3		8.3	11.2	1.0	13.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{OSHL}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSLH}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

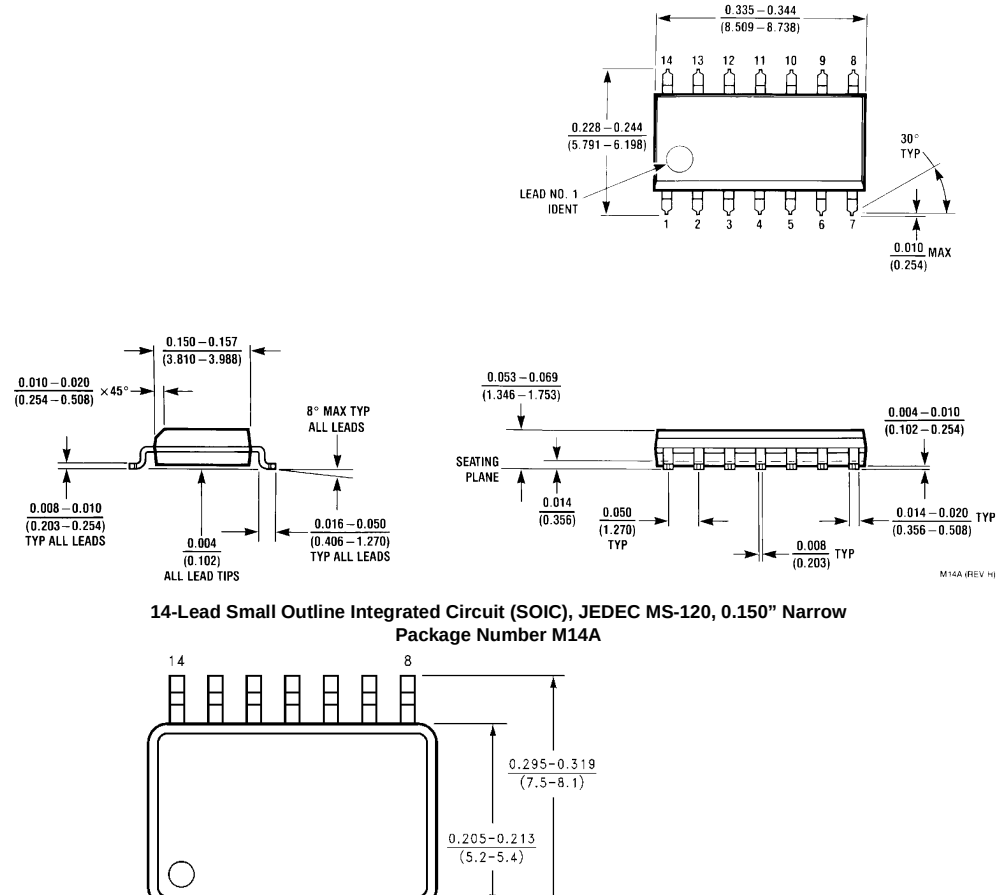
Capacitance

Symbol	Parameter	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4.0	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		14				pF

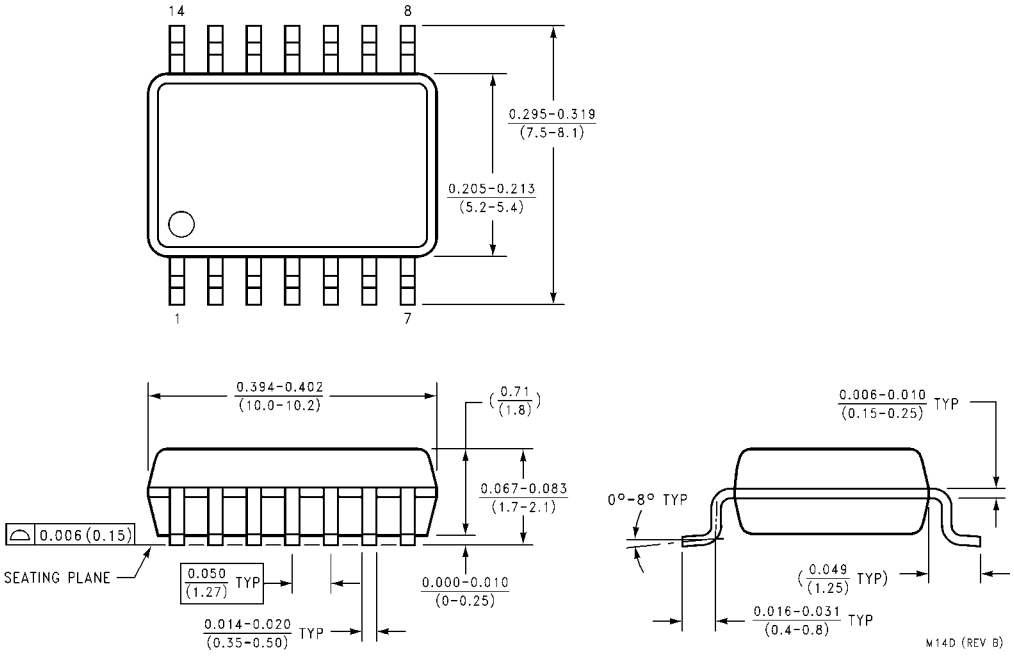
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per bit)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

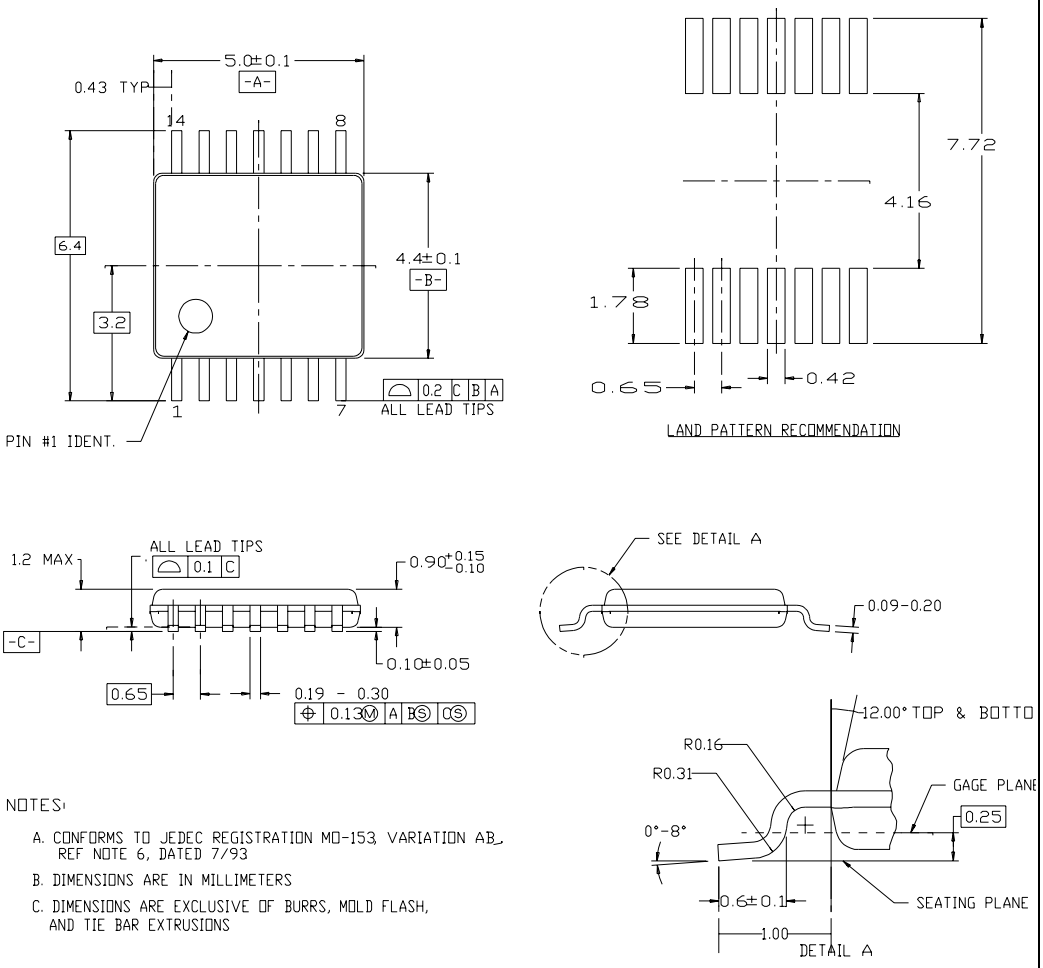


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

October 1996
Revised March 1999

74LVX132
Low Voltage Quad 2-Input NAND Schmitt Trigger

General Description

The LVX132 contains four 2-input NAND Schmitt Trigger Gates. The pin configuration and function are the same as the LVX00 but the inputs have hysteresis between the positive-going and negative-going input thresholds, which are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals, thus providing greater noise margins than conventional gates.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

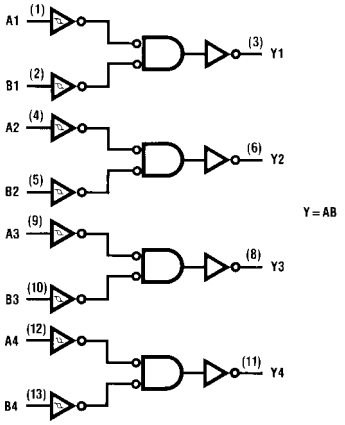
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

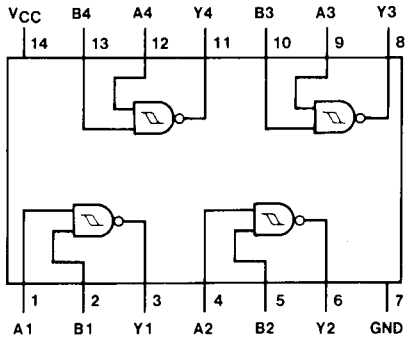
Order Number	Package Number	Package Description
74LVX132M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX132SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX132MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Diagram



Connection Diagram



Pin Descriptions

Pin Names	Descriptions
A_n, B_n	Inputs
Y_n	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{t+}	Positive Threshold	3.0			2.2		2.2	V		
V_{t-}	Negative Threshold	3.0	0.9			0.9		V		
V_H	Hysteresis	3.0	0.3		1.2	0.3	1.2	V		
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		7.0	11.5	1.0	13.0	ns	15
t_{PHL}	Delay Time			10.5	16.0	1.0	18.7		50
		3.3 ± 0.3		6.1	10.6	1.0	12.5		15
				9.0	15.4	1.0	17.5		50
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

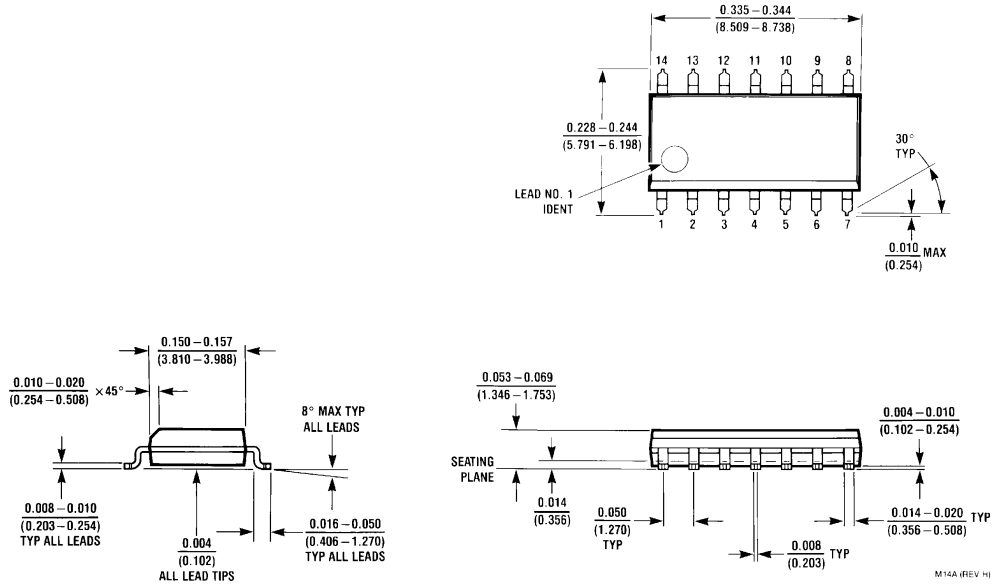
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		18				pF

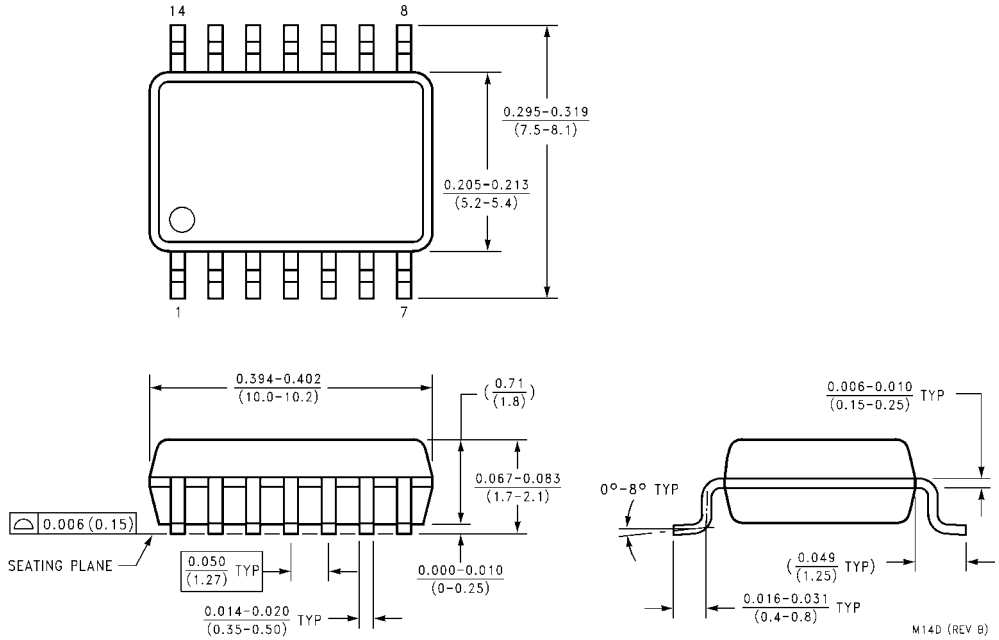
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{6 \text{ (per Gate)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

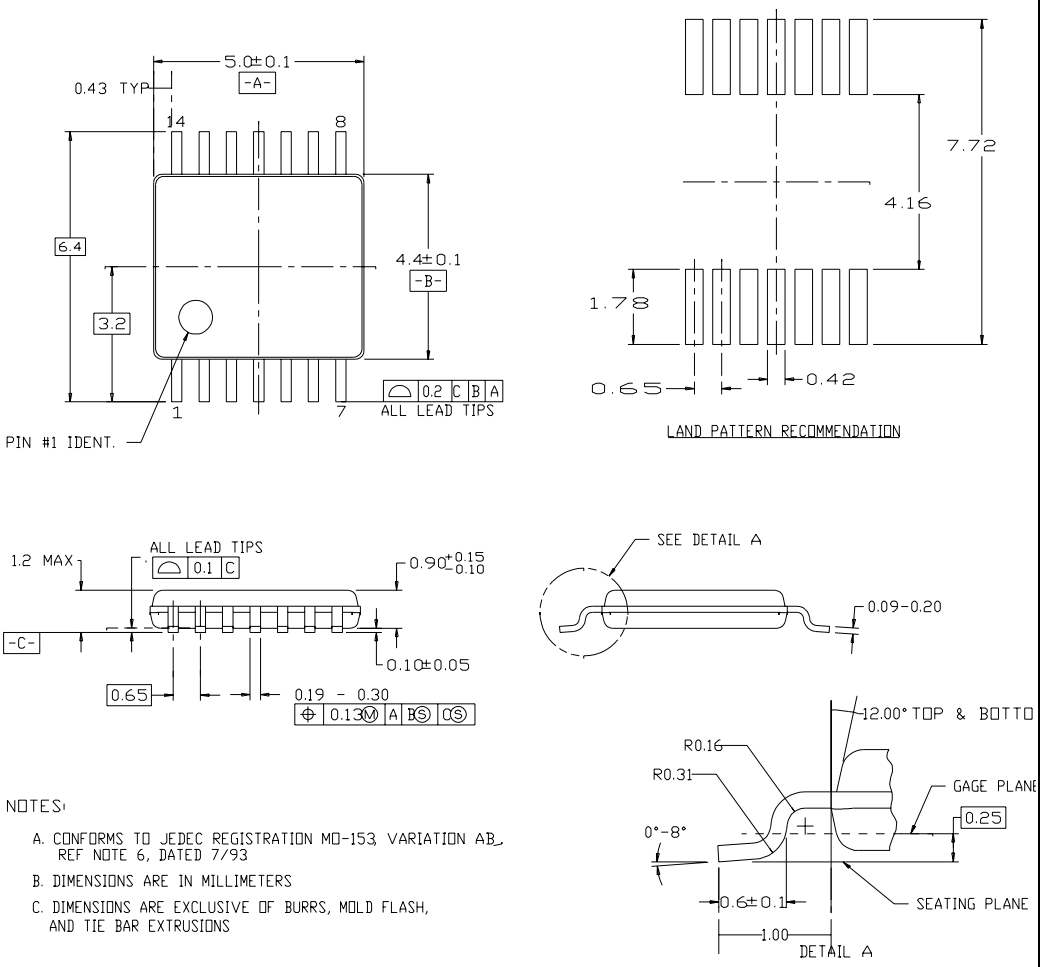


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

June 1993
Revised March 1999

74LVX138
Low Voltage 1-of-8 Decoder/Demultiplexer

General Description

The LVX138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed bipolar memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three LVX138 devices or a 1-of-32 decoder using four LVX138 devices and one inverter.

Features

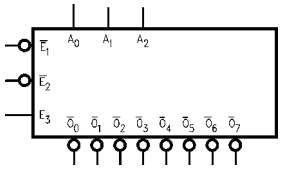
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

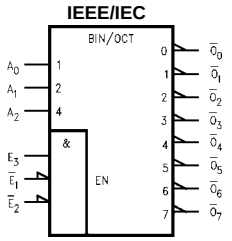
Order Number	Package Number	Package Description
74LVX138M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX138MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

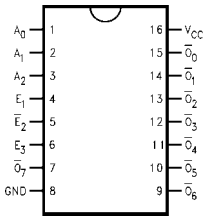
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_2	Address Inputs
$\overline{E}_1$–$\overline{E}_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0$–$\overline{O}_7$	Outputs

Functional Description

The LVX138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A_0, A_1, A_2) and, when enabled, provides eight mutually exclusive active-LOW outputs ($\overline{O}_0$–$\overline{O}_7$). The LVX138 features three Enable inputs, two active-LOW ($\overline{E}_1$, $\overline{E}_2$) and one active-HIGH (E_3).

All outputs will be HIGH unless $\overline{E}_1$ and $\overline{E}_2$ are LOW and E_3 is HIGH.

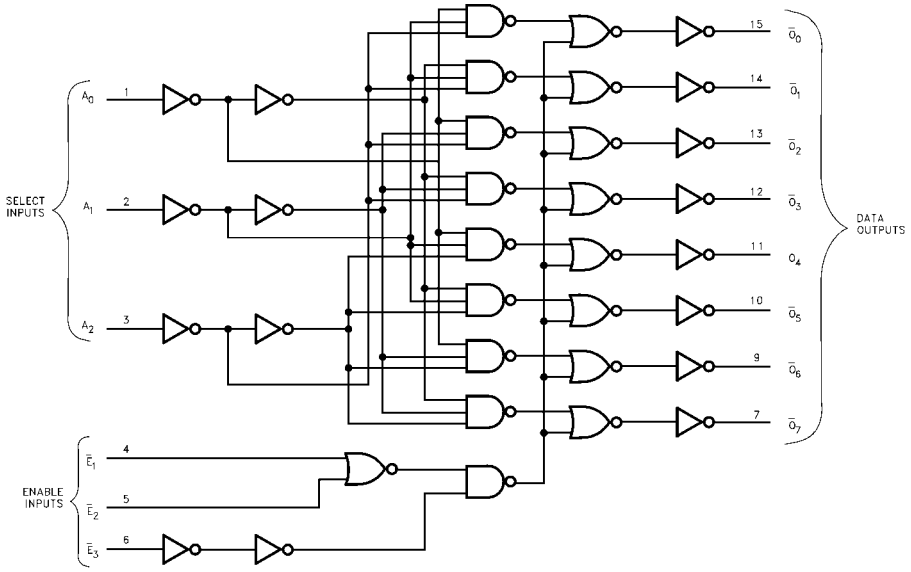
The LVX138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active-HIGH or active-LOW state.

Truth Table

Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	CL (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		7.1	13.8	1.0	16.5	ns	15
t_{PHL}	Delay Time			9.6	17.3	1.0	20.0		50
	A_n to $\overline{O}_n$	3.3 ± 0.3		5.5	8.8	1.0	10.5		15
				8.0	12.3	1.0	14.0		50
t_{PLH}	Propagation	2.7		8.8	16.0	1.0	18.5	ns	15
t_{PHL}	Delay Time			11.3	19.5	1.0	22.0		50
	$\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$	3.3 ± 0.3		6.9	10.4	1.0	11.5		15
				9.4	13.9	1.0	15.0		50
t_{PLH}	Propagation	2.7		8.7	16.3	1.0	19.5	ns	15
t_{PHL}	Delay Time			11.2	19.8	1.0	23.0		50
	E_3 to $\overline{O}_n$	3.3 ± 0.3		6.8	10.6	1.0	12.5		15
				9.3	14.1	1.0	16.0		50
t_{OSHL}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSLH}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

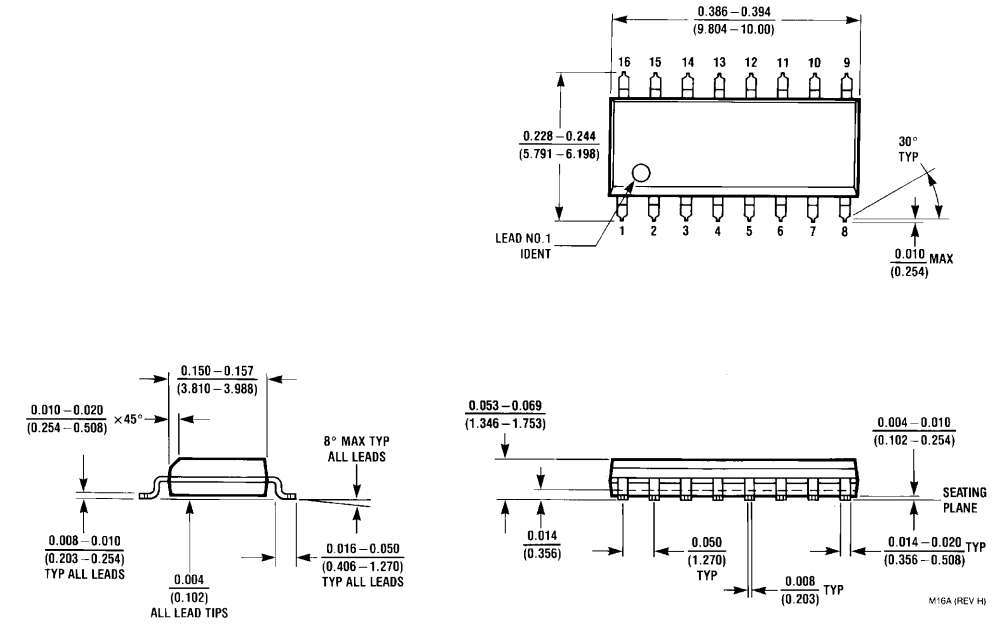
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		34				pF

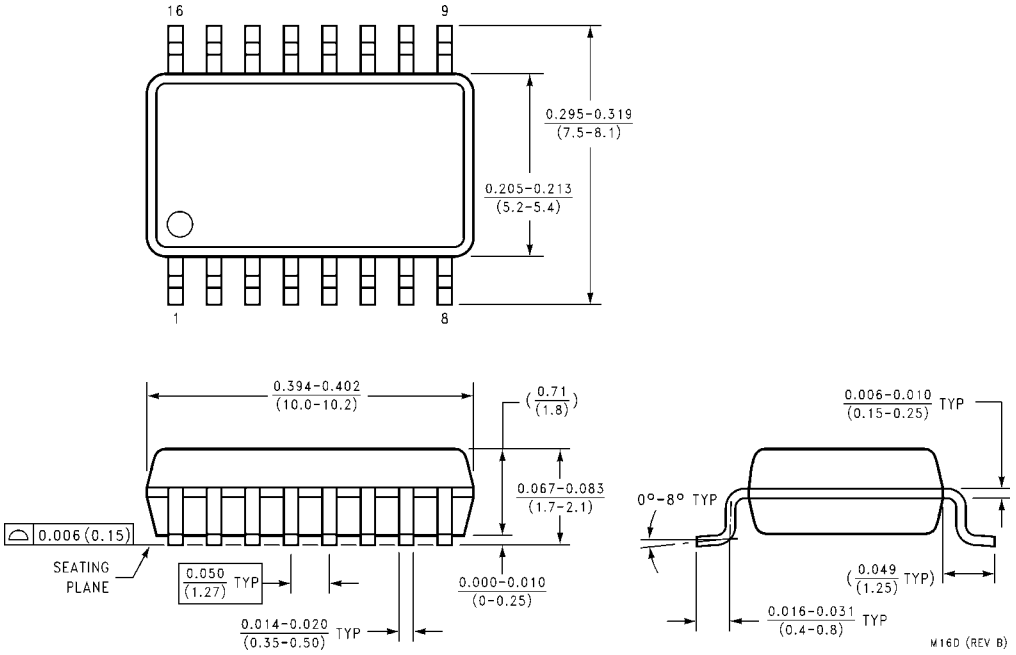
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $C_{PD} \times V_{CC} \times I_{IN} + I_{CC}$

Physical Dimensions inches (millimeters) unless otherwise noted

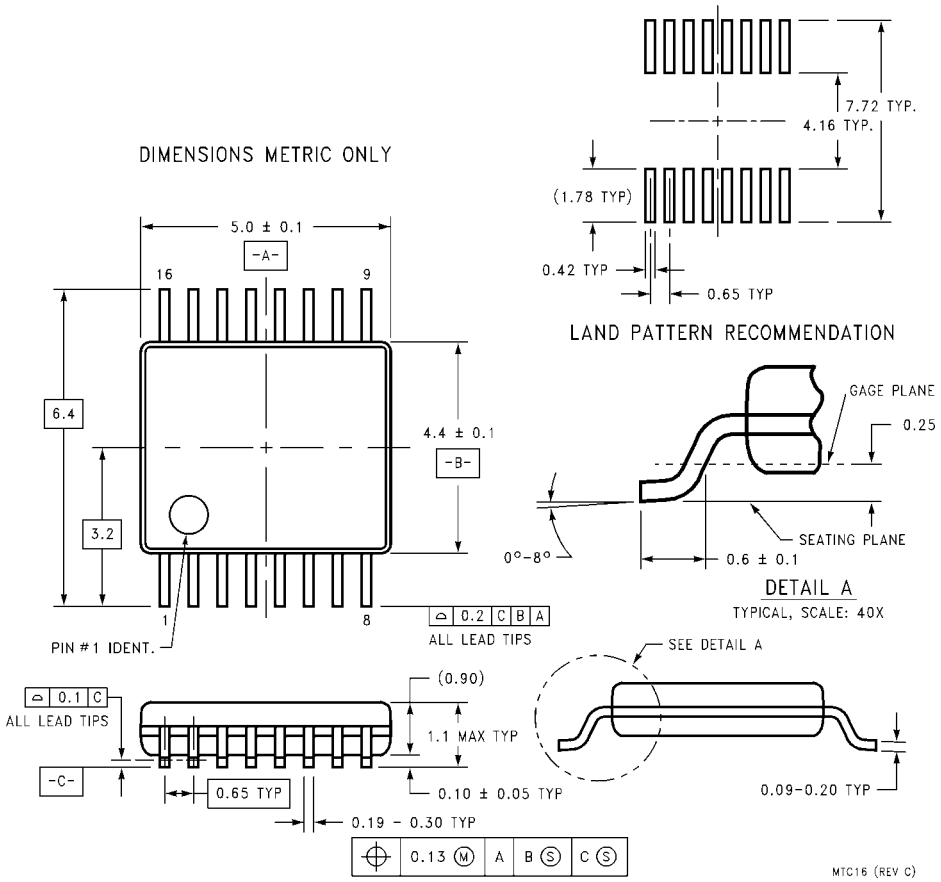


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP) EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1993
Revised December 1999

74LVX14
Low Voltage Hex Inverter with Schmitt Trigger Input

General Description

The LVX14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVX14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

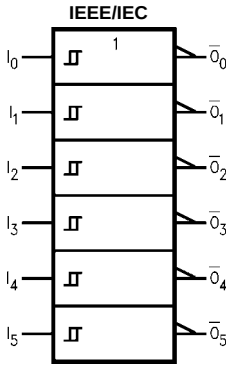
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

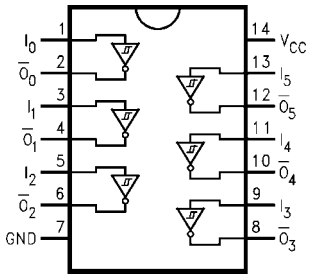
Order Number	Package Number	Package Description
74LVX14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
I_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

Input	Output
A	$\overline{\mathbf{O}}$
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{t+}	Positive Threshold	3.0			2.2		2.2	V		
V_{t-}	Negative Threshold	3.0	0.9			0.9		V		
V_H	Hysteresis	3.0	0.3		1.2	0.3	1.2	V		
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9				I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V	V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1			I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V	V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		8.7	16.3	1.0	19.5	ns	15
t_{PHL}	Delay Time			11.2	19.8	1.0	23.0		50
		3.3 ± 0.3		6.8	10.6	1.0	12.5		15
				9.3	14.1	1.0	16.0		50
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

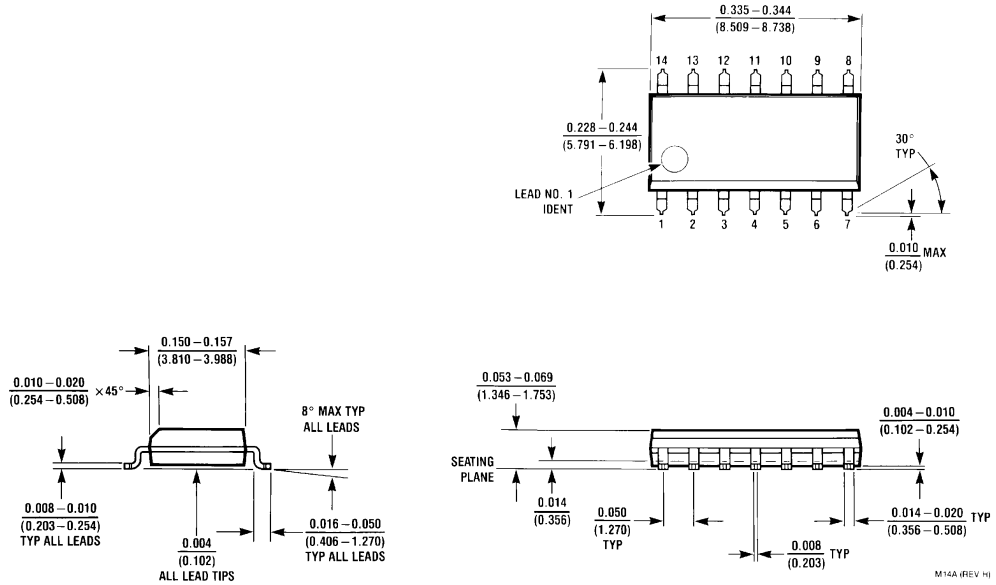
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		21				pF

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

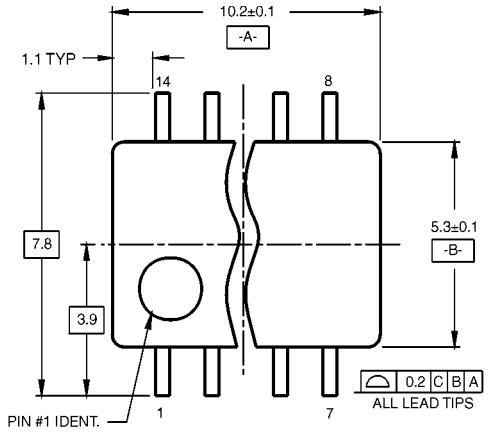
Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{6 \text{ (per Gate)}}$

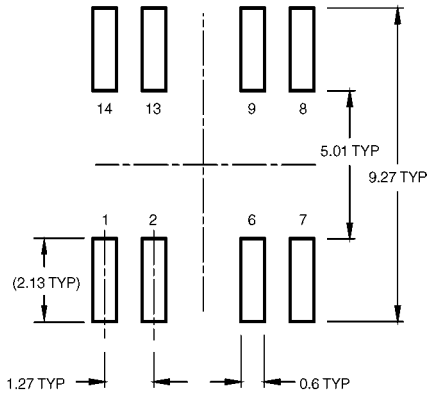
Physical Dimensions inches (millimeters) unless otherwise noted



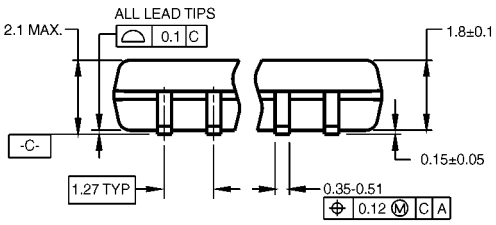
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A

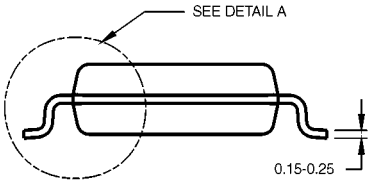
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



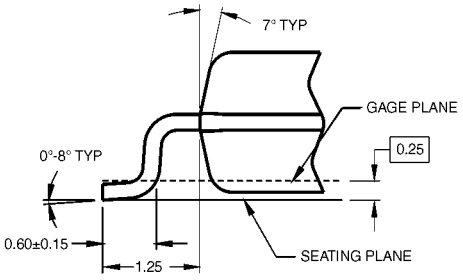


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

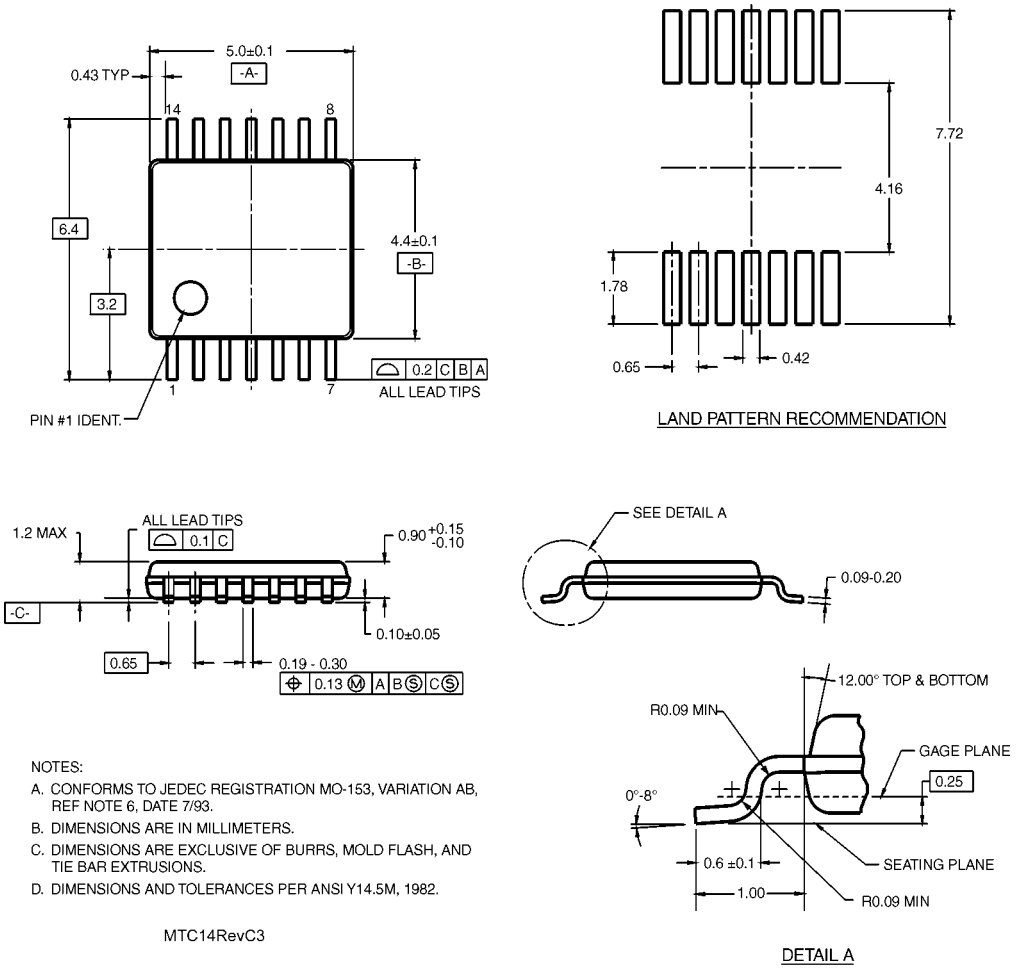
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1

14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX157
Low Voltage Quad 2-Input Multiplexer

General Description

The LVX157 is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (noninverted) form. The LVX157 can also be used as a function generator.

Features

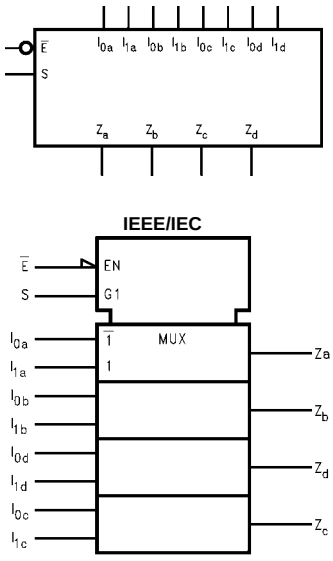
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

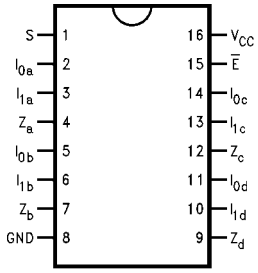
Order Number	Package Number	Package Description
74LVX157M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX157SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX157MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices are also available in Tape and Reel. Specify by appending letter suffix "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{E}$	Enable Input
S	Select Input
Z_a–Z_d	Outputs

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Functional Description

The LVX157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\overline{E}$) is active-LOW. When $\overline{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The LVX157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$Z_a = \overline{E} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$

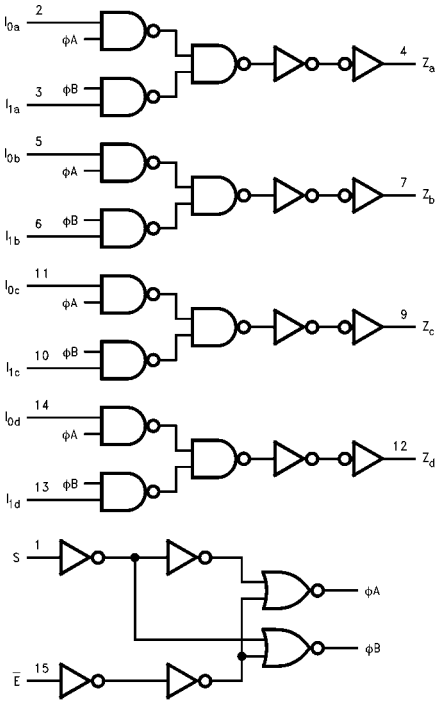
$Z_b = \overline{E} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$

$Z_c = \overline{E} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$

$Z_d = \overline{E} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$

A common use of the LVX157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The LVX157 can generate any four of the sixteen different functions of two variables with one variable common. This is useful for implementing gating functions.

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		6.6	12.5	1.0	15.5	ns	15
t_{PHL}	Delay Time			9.1	16.0	1.0	19.0		50
	I_n to Z_n	3.3 ± 0.3		5.1	7.9	1.0	9.5		15
				7.6	11.4	1.0	13.0		50
t_{PLH}	Propagation	2.7		8.9	16.9	1.0	20.5	ns	15
t_{PHL}	Delay Time			11.4	20.4	1.0	24.0		50
	S to Z_n	3.3 ± 0.3		7.0	11.0	1.0	13.0		15
				9.5	14.5	1.0	16.5		50
t_{PLH}	Propagation	2.7		9.1	17.6	1.0	20.5	ns	15
t_{PHL}	Delay Time			11.6	21.1	1.0	24.0		50
	$\overline{E}$ to Z_n	3.3 ± 0.3		7.2	11.5	1.0	13.5		15
				9.7	15.0	1.0	17.0		50
t_{OSHL}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSLH}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design.

$t_{OSLH} = |t_{PLHm} - t_{PLHn}|$.

$t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.

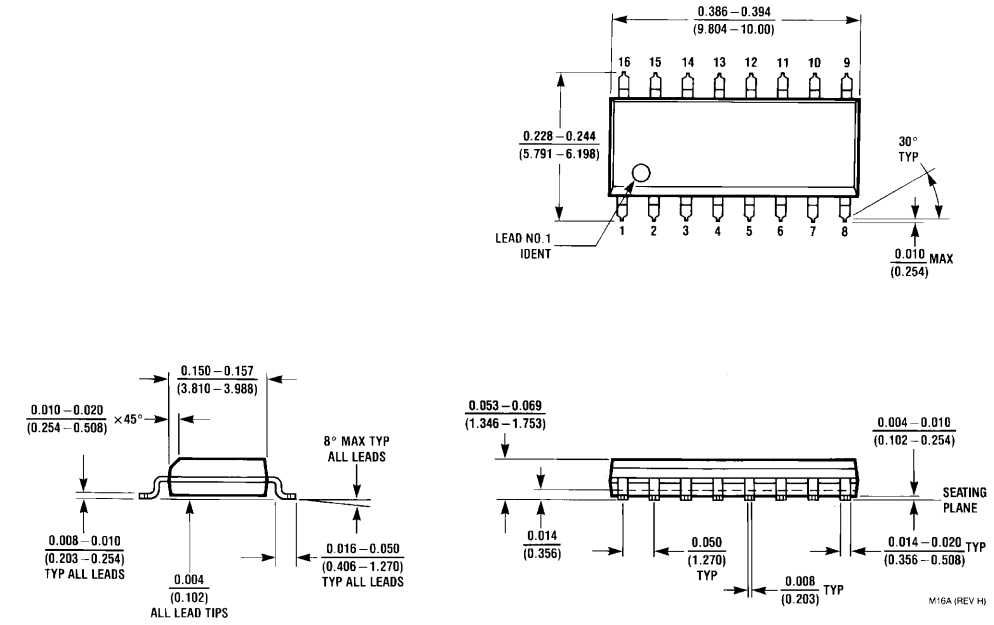
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		20				pF

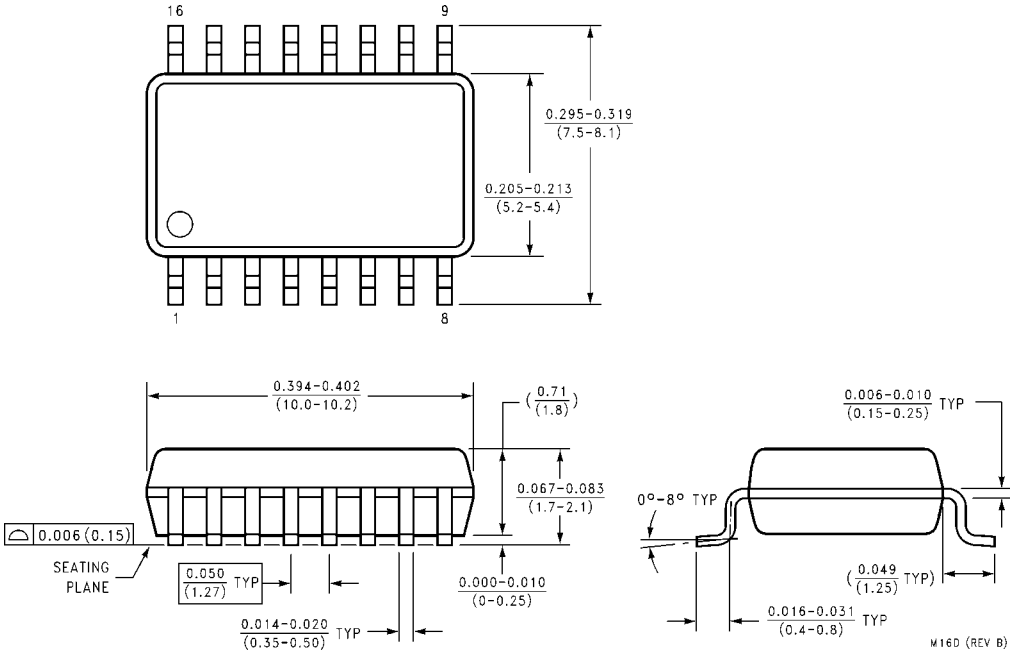
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

Physical Dimensions inches (millimeters) unless otherwise noted

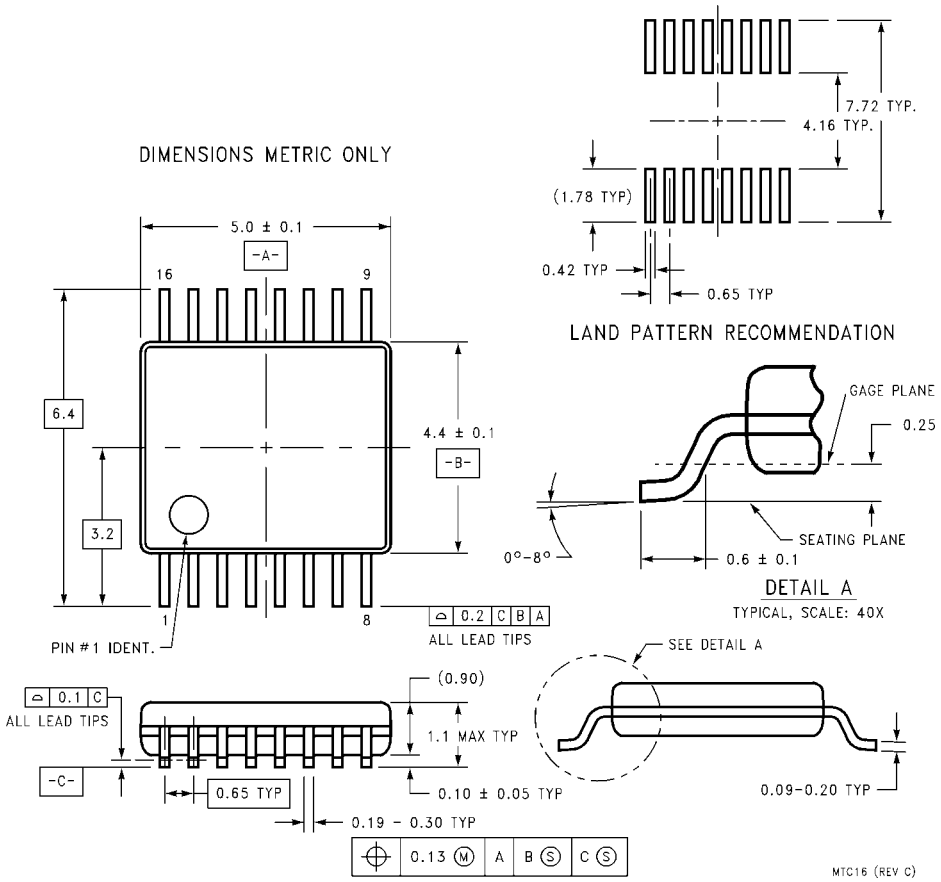


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

FAIRCHILD SEMICONDUCTOR™

January 1999
Revised June 1999

74LVX161284
Low Voltage IEEE 161284 Translating Transceiver

General Description

The LVX161284 contains eight bidirectional data buffers and eleven control/status buffers to implement a full IEEE 1284 compliant interface. The device supports the IEEE 1284 standard and is intended to be used in an Extended Capabilities Port mode (ECP). The pinout allows for easy connection from the Peripheral (A-side) to the Host (cable side).

Outputs on the cable side can be configured to be either open drain or high drive (± 14 mA) and are connected to a separate power supply pin (V_{CC}—cable) to allow these outputs to be driven by a higher supply voltage than the A-side. The pull-up and pull-down series termination resistance of these outputs on the cable side is optimized to drive an external cable. In addition, all inputs (except HLH) and outputs on the cable side contain internal pull-up resistors connected to the V_{CC}—cable supply to provide proper termination and pull-ups for open drain mode.

Outputs on the Peripheral side are standard low-drive CMOS outputs designed to interface with 3V logic. The DIR input controls data flow on the A_1–A_8/B_1–B_8 transceiver pins.

Features

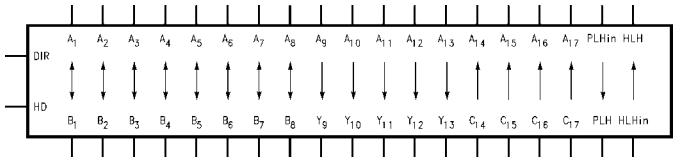
- Supports IEEE 1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals
- Translation capability allows outputs on the cable side to interface with 5V signals
- All inputs have hysteresis to provide noise margin
- B and Y output resistance optimized to drive external cable
- B and Y outputs in high impedance mode during power down
- Inputs and outputs on cable side have internal pull-up resistors
- Flow-through pin configuration allows easy interface between the “Peripheral and Host”
- Replaces the function of two (2) 74ACT1284 devices

Ordering Code

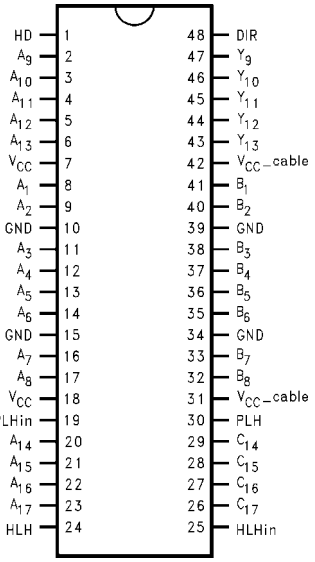
Order Number	Package Number	Package Description
74LVX161284MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300” Wide
74LVX161284MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
HD	High Drive Enable Input (Active High)
DIR	Direction Control Input
A_1–A_8	Inputs or Outputs
B_1–B_8	Inputs or Outputs
A_9–A_{13}	Inputs
Y_9–Y_{13}	Outputs
A_{14}–A_{17}	Outputs
C_{14}–C_{17}	Inputs
PLH_{IN}	Peripheral Logic High Input
PLH	Peripheral Logic High Output
HLH_{IN}	Host Logic High Input
HLH	Host Logic High Output

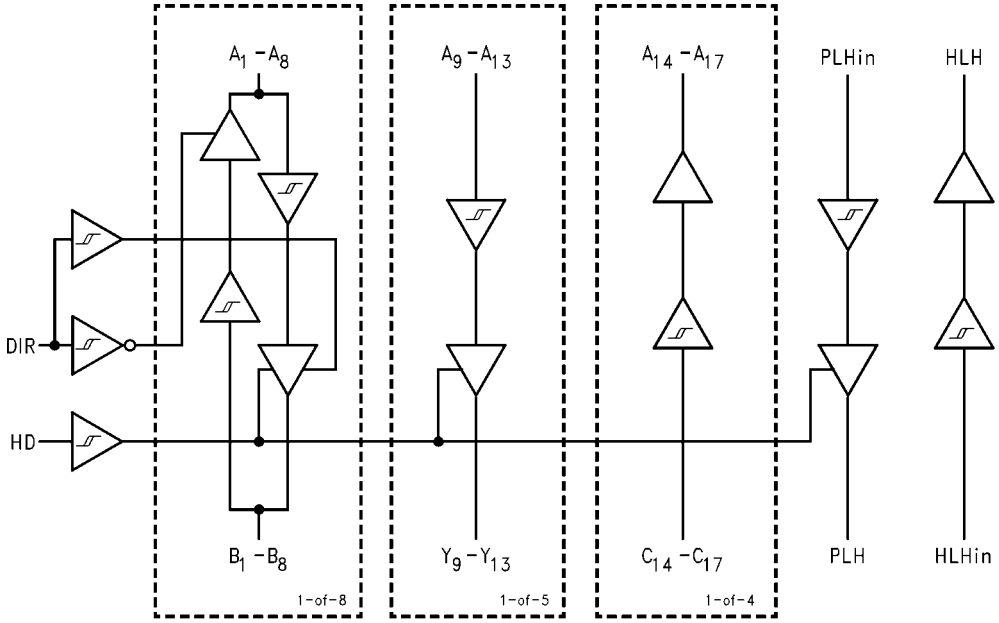
Truth Table

Inputs		Outputs
DIR	HD	
L	L	B_1–B_8 Data to A_1–A_8, and
		A_9–A_{13} Data to Y_9–Y_{13} (Note 1)
		C_{14}–C_{17} Data to A_{14}–A_{17}
		PLH Open Drain Mode
L	H	B_1–B_8 Data to A_1–A_8, and
		A_9–A_{13} Data to Y_9–Y_{13}
		C_{14}–C_{17} Data to A_{14}–A_{17}
H	L	A_1–A_8 Data to B_1–B_8 (Note 2)
		A_9–A_{13} Data to Y_9–Y_{13} (Note 1)
		C_{14}–C_{17} Data to A_{14}–A_{17}
		PLH Open Drain Mode
H	H	A_1–A_8 Data to B_1–B_8
		A_9–A_{13} Data to Y_9–Y_{13}
		C_{14}–C_{17} Data to A_{14}–A_{17}

Note 1: Y_9–Y_{13} Open Drain Outputs

Note 2: B_1–B_8 Open Drain Outputs

Logic Diagram



Absolute Maximum Ratings(Note 3)

Supply Voltage

V_{CC}	−0.5V to +4.6V
$V_{CC—Cable}$	−0.5V to +7.0V
$V_{CC—Cable}$ Must Be ≥ V_{CC}	

Input Voltage (V_I)—(Note 4)

A_1–A_{13}, PLH_{IN}, DIR, HD	−0.5V to V_{CC} + 0.5V
B_1–B_8, C_{14}–C_{17}, HLH_{IN}	−0.5V to +5.5V (DC)
B_1–B_8, C_{14}–C_{17}, HLH_{IN}	−2.0V to +7.0V*
	*40 ns Transient

Output Voltage (V_O)

A_1–A_8, A_{14}–A_{17}, HLH	−0.5V to V_{CC} +0.5V
B_1–B_8, Y_9–Y_{13}, PLH	−0.5V to +5.5V (DC)
B_1–B_8, Y_9–Y_{13}, PLH	−2.0V to +7.0V*
	*40 ns Transient

DC Output Current (I_O)

A_1–A_8, HLH	±25 mA
B_1–B_8, Y_9–Y_{13}	±50 mA
PLH (Output LOW)	84 mA
PLH (Output HIGH)	−50 mA

Input Diode Current (I_{IK})—(Note 4)

DIR, HD, A_9–A_{13}, PLH, HLH, C_{14}–C_{17}	−20 mA

Output Diode Current (I_{OK})

A_1–A_8, A_{14}–A_{17}, HLH	±50 mA
B_1–B_8, Y_9–Y_{13}, PLH	−50 mA

DC Continuous V_{CC} or Ground Current	±200 mA
Storage Temperature	−65°C to +150°C
ESD (HBM) Last Passing Voltage	2000V

Recommended Operating Conditions

Supply Voltage	
V_{CC}	3.0V to 3.6V
$V_{CC—Cable}$	3.0V to 5.5V
DC Input Voltage (V_I)	0V to V_{CC}
Open Drain Voltage (V_O)	0V to 5.5V
Operating Temperature (T_A)	−40°C to +85°C

Note 3: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Fairchild does not recommend operation outside the databook specifications.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$V_{CC—Cable}$ (V)	T_A = 0°C to +70°C	T_A = −40°C to +85°C	Units	Conditions
					Guaranteed Limits			
V_{IK}	Input Clamp Diode Voltage		3.0	3.0	−1.2	−1.2	V	I_I = −18 mA
V_{IH}	Minimum High Level Input Voltage	A_n, B_n, PLH_{IN}, DIR, HD	3.0–3.6	3.0–5.5	2.0	2.0	V	
		C_n	3.0–3.6	3.0–5.5	2.3	2.3		
		HLH_{IN}	3.0–3.6	3.0–5.5	2.6	2.6		
V_{IL}	Maximum Low Level Input Voltage	A_n, B_n, PLH_{IN}, DIR, HD	3.0–3.6	3.0–5.5	0.8	0.8	V	
		C_n	3.0–3.6	3.0–5.5	0.8	0.8		
		HLH_{IN}	3.0–3.6	3.0–5.5	1.6	1.6		
ΔV_T	Minimum Input Hysteresis	A_n, B_n, PLH_{IN}, DIR, HD	3.3	5.0	0.4	0.4	V	V_T^+–V_T^-
		C_n	3.3	5.0	0.8	0.8		V_T^+–V_T^-
		HLH_{IN}	3.3	5.0	0.2	0.2		V_T^+–V_T^-
V_{OH}	Minimum High Level Output Voltage	A_n, HLH	3.0	3.0	2.8	2.8	V	I_{OH} = −50 μA
			3.0	3.0	2.4	2.4		I_{OH} = −4 mA
		B_n, Y_n	3.0	3.0	2.0	2.0		I_{OH} = −14 mA
		B_n, Y_n	3.0	4.5	2.23	2.23		I_{OH} = −14 mA
		PLH	3.15	3.15	3.1	3.1		I_{OH} = −500 μA
V_{OL}	Maximum Low Level Output Voltage	A_n, HLH	3.0	3.0	0.2	0.2	V	I_{OL} = 50 μA
			3.0	3.0	0.4	0.4		I_{OL} = 4 mA
		B_n, Y_n	3.0	3.0	0.8	0.8		I_{OL} = 14 mA
		B_n, Y_n	3.0	4.5	0.77	0.77		I_{OL} = 14 mA
		PLH	3.0	3.0	0.85	0.95		I_{OL} = 84 mA
		PLH	3.0	4.5	0.8	0.9		I_{OL} = 84 mA
R_D	Maximum Output Impedance	B_1–B_8, Y_9–Y_{13}	3.3	3.3	60	60	Ω	(Note 5) (Note 7)
			3.3	5.0	55	55		
	Minimum Output Impedance	B_1–B_8, Y_9–Y_{13}	3.3	3.3	30	30		(Note 5) (Note 7)
			3.3	5.0	35	35		

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CC} (V)	$V_{CC—Cable}$ (V)	$T_A = 0°C$ to $+70°C$	$T_A = -40°C$ to $+85°C$	Units	Conditions
					Guaranteed Limits			
R_P	Maximum Pull-Up	B_1–B_8, Y_9–Y_{13},	3.3	3.3	1650	1650	Ω	
	Resistance	C_{14}–C_{17}	3.3	5.0	1650	1650		
	Minimum Pull-Up	B_1–B_8, Y_9–Y_{13}	3.3	3.3	1150	1150	Ω	
	Resistance	C_{14}–C_{17}	3.3	5.0	1150	1150		
I_{IH}	Maximum Input	A_9–A_{13}, PLH_{IN},	3.6	3.6	1.0	1.0	µA	$V_I = 3.6V$
	Current in	HD, DIR, HLH_{IN}						
	High State	C_{14}–C_{17}	3.6	3.6	50.0	50.0		$V_I = 3.6V$
		C_{14}–C_{17}	3.6	5.5	100	100		$V_I = 5.5V$
I_{IL}	Maximum Input	A_9–A_{13}, PLH_{IN},	3.6	3.6	−1.0	−1.0	µA	$V_I = 0.0V$
	Current in	HD, DIR, HLH_{IN}						
	Low State	C_{14}–C_{17}	3.6	3.6	−3.5	−3.5	mA	$V_I = 0.0V$
		C_{14}–C_{17}	3.6	5.5	−5.0	−5.0	mA	$V_I = 0.0V$
I_{OZH}	Maximum Output	A_1–A_8	3.6	3.6	20	20	µA	$V_O = 3.6V$
	Disable Current	B_1–B_8	3.6	3.6	50	50	µA	$V_O = 3.6V$
	(High)	B_1–B_8	3.6	5.5	100	100	µA	$V_O = 5.5V$
I_{OZL}	Maximum	A_1–A_8	3.6	3.6	−20	−20	µA	$V_O = 0.0V$
	Output Disable	B_1–B_8	3.6	3.6	−3.5	−3.5	mA	
	Current (Low)	B_1–B_8	3.6	5.5	−5.0	−5.0	mA	
I_{OFF}	Power Down	B_1–B_8, Y_9–Y_{13},	0.0	0.0	100	100	µA	$V_O = 5.5V$
	Output Leakage	PLH						
I_{OFF}	Power Down	C_{14}–C_{17}, HLH_{IN}	0.0	0.0	100	100	µA	$V_I = 5.5V$
	Input Leakage							
$I_{OFF—ICC}$	PowerDown		0.0	0.0	250	250	µA	(Note 6)
	Leakage to V_{CC}							
$I_{OFF—ICC2}$	Power Down Leakage		0.0	0.0	250	250	µA	(Note 6)
	to $V_{CC—Cable}$							
I_{CC}	Maximum Supply		3.6	3.6	45	45	mA	$V_I = V_{CC}$ or GND
	Current		3.6	5.5	70	70	mA	$V_I = V_{CC}$ or GND

Note 5: Output impedance is measured with the output active low and active high (HD = high).

Note 6: Power-down leakage to V_{CC} or $V_{CC—Cable}$ is tested by simultaneously forcing all pins on the cable-side (B_1–B_8, Y_9–Y_{13}, PLH, C_{14}–C_{17} and HLH_{IN}) to 5.5V and measuring the resulting I_{CC} or $I_{CC—Cable}$.

Note 7: This parameter is guaranteed but not tested, characterized only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = 0°C$ to $+70°C$, $V_{CC} = 3.0V–3.6V$, $V_{CC—Cable} = 3.0V–5.5V$		$T_A = -40°C$ to $+85°C$, $V_{CC} = 3.0V–3.6V$, $V_{CC—Cable} = 3.0V–5.5V$		Units	Fig. No.
		Min	Max	Min	Max		
t_{PHL}	$A_1–A_8$ to $B_1–B_8$	2.0	40.0	2.0	44.0	ns	1
t_{PLH}	$A_1–A_8$ to $B_1–B_8$	2.0	40.0	2.0	44.0	ns	2
t_{PHL}	$B_1–B_8$ to $A_1–A_8$	2.0	40.0	2.0	44.0	ns	3
t_{PLH}	$B_1–B_8$ to $A_1–A_8$	2.0	40.0	2.0	44.0	ns	3
t_{PHL}	$A_9–A_{13}$ to $Y_9–Y_{13}$	2.0	40.0	2.0	44.0	ns	1
t_{PLH}	$A_9–A_{13}$ to $Y_9–Y_{13}$	2.0	40.0	2.0	44.0	ns	2
t_{PHL}	$C_{14}–C_{17}$ to $A_{14}–A_{17}$	2.0	40.0	2.0	44.0	ns	3
t_{PLH}	$C_{14}–C_{17}$ to $A_{14}–A_{17}$	2.0	40.0	2.0	44.0	ns	3
t_{SKEW}	LH-LH or HL-HL		10.0		12.0	ns	(Note 9)
t_{PHL}	PLH_{IN} to PLH	2.0	40.0	2.0	44.0	ns	1
t_{PLH}	PLH_{IN} to PLH	2.0	40.0	2.0	44.0	ns	2
t_{PHL}	HLH_{IN} to HLH	2.0	40.0	2.0	44.0	ns	3
t_{PLH}	HLH_{IN} to HLH	2.0	40.0	2.0	44.0	ns	3
t_{PHZ}	Output Disable Time	2.0	15.0	2.0	18.0	ns	7
t_{PLZ}	DIR to $A_1–A_8$	2.0	15.0	2.0	18.0		
t_{PZH}	Output Enable Time	2.0	50.0	2.0	50.0	ns	8
t_{PZL}	DIR to $A_1–A_8$	2.0	50.0	2.0	50.0		
t_{PHZ}	Output Disable Time	2.0	50.0	2.0	50.0	ns	9
t_{PLZ}	DIR to $B_1–B_8$	2.0	50.0	2.0	50.0		
t_{pEN}	Output Enable Time	2.0	25.0	2.0	28.0	ns	2
	HD to $B_1–B_8$, $Y_9–Y_{13}$	2.0	25.0	2.0	28.0		
t_{pDIS}	Output Disable Time	2.0	25.0	2.0	28.0	ns	2
	HD to $B_1–B_8$, $Y_9–Y_{13}$	2.0	25.0	2.0	28.0		
$t_{pEN}–t_{pDIS}$	Output Enable-Output Disable		10.0		12.0	ns	
t_{SLEW}	Output Slew Rate						
t_{PLH}	$B_1–B_8$, $Y_9–Y_{13}$	0.05	0.40	0.05	0.40	V/ns	5
t_{PHL}		0.05	0.40	0.05	0.40		4
t_r, t_f	t_{RISE} and t_{FALL}		120		120	ns	6
	$B_1–B_8$(Note 8), $Y_9–Y_{13}$(Note 8)		120		120		(Note 10)

Note 8: Open Drain

Note 9: t_{SKEW} is measured for common edge output transitions and compares the measured propagation delay for a given path type:

(i) $A_1–A_8$ to $B_1–B_8$, $A_9–A_{13}$ to $Y_9–Y_{13}$

(ii) $B_1–B_8$ to $A_1–A_8$

(iii) $C_{14}–C_{17}$ to $A_{14}–A_{17}$

Note 10: This parameter is guaranteed but not tested, characterized only.

Note 11: Pulse Generator for all pulses; Rate ≤1.0 MHz; $Z_O \leq 50\Omega$; $t_f \leq 2.5$ ns, $t_r \leq 2.5$ ns.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	3	pF	$V_{CC} = 0.0V$ (HD, DIR, $A_9–A_{13}$, $C_{14}–C_{17}$, PLH_{IN} and HLH_{IN})
$C_{I/O}$ (Note 12)	I/O Pin Capacitance	5	pF	$V_{CC} = 3.3V$

Note 12: $C_{I/O}$ is measured at frequency = 1 MHz, per MIL-STD-883B, Method 3012

AC Loading and Waveforms

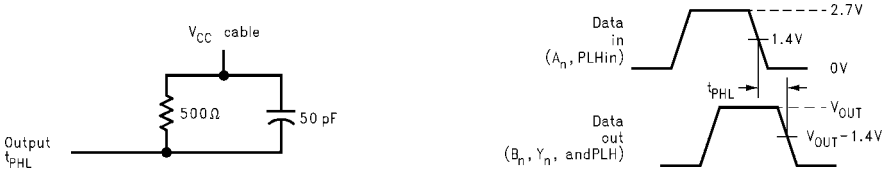


FIGURE 1. t_{PHL} Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}
PLHin to PLH

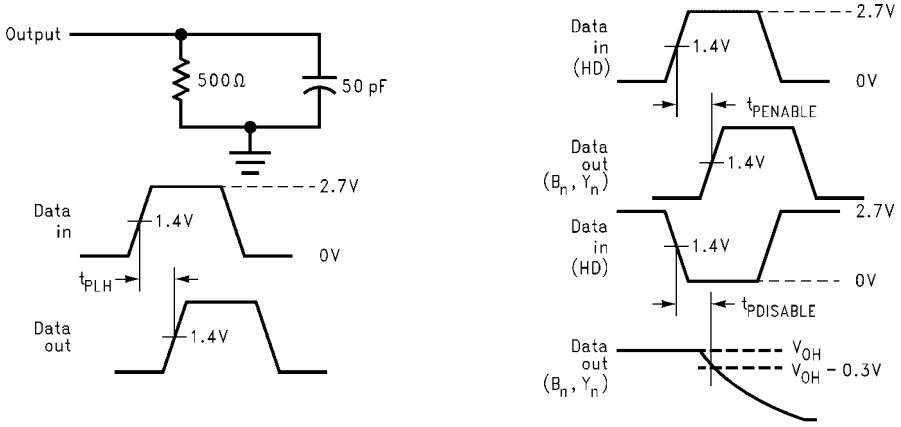


FIGURE 2. t_{PLH}, t_{pEn}, t_{pDis} Test Load and Waveforms
A_1–A_8 to B_1–B_8, A_9–A_{13} to Y_9–Y_{13}
PLHin to PLH, HD to B_1–B_8, Y_9–Y_{13}, PLH

V_{MO} = 50% V_{CC}

FIGURE 3. t_{PHL}, t_{PLH} Test Load and Waveforms
B_1–B_8 to A_1–A_8, C_{14}–C_{17} to A_{14}–A_{17}, HLHin to HLH

AC Loading and Waveforms (Continued)

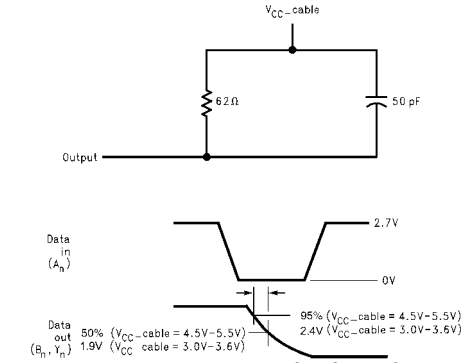


FIGURE 4. t_{SLEW} HL Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}

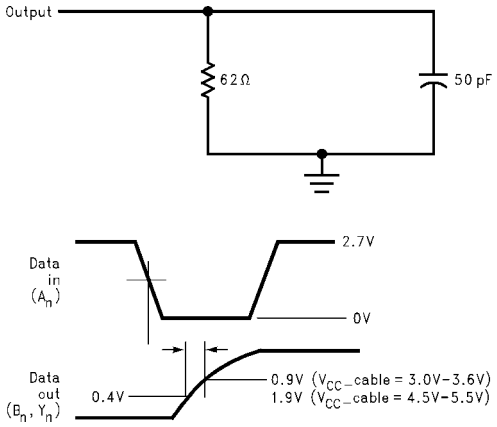
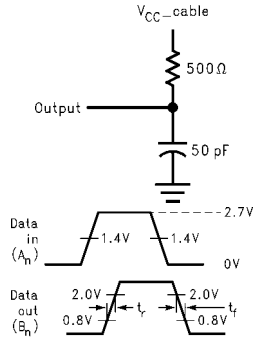


FIGURE 5. t_{SLEW} LH Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}

AC Loading and Waveforms (Continued)



t_r = Output Rise Time, Open Drain

t_f = Output Fall Time, Open Drain

FIGURE 6. t_{RISE} and t_{FALL} Test Load and Waveforms for Open Drain Outputs A_1–A_8 to B_1–B_8, A_9–A_{13} to Y_9–Y_{13}

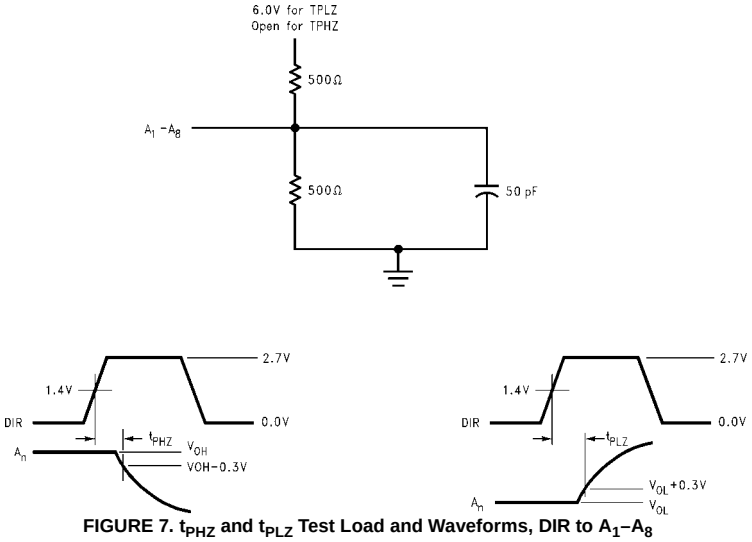


FIGURE 7. t_{PHZ} and t_{PLZ} Test Load and Waveforms, DIR to A_1–A_8

AC Loading and Waveforms (Continued)

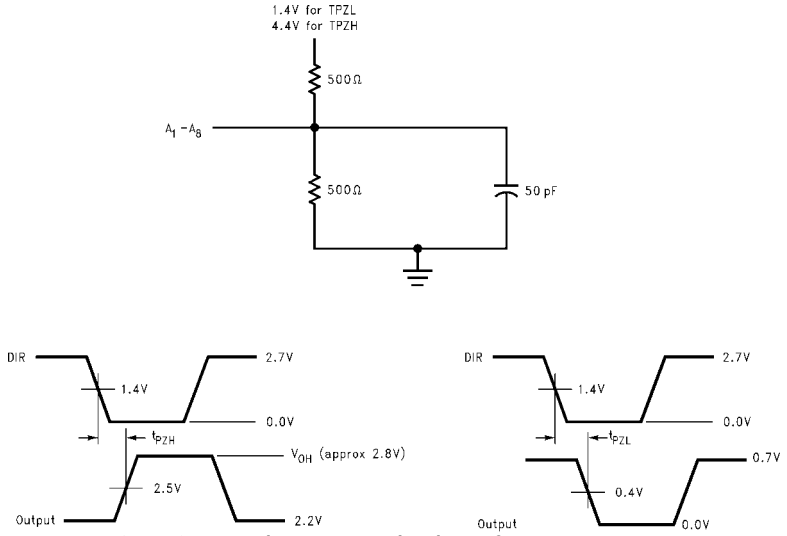


FIGURE 8. t_{PZH} and t_{PZL} Test Load and Waveforms, DIR to A_1–A_8

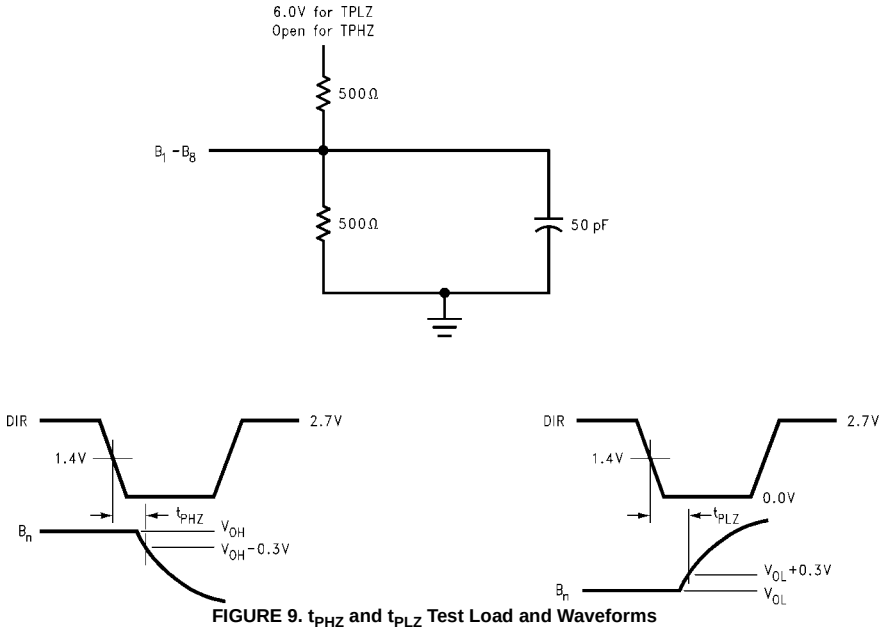
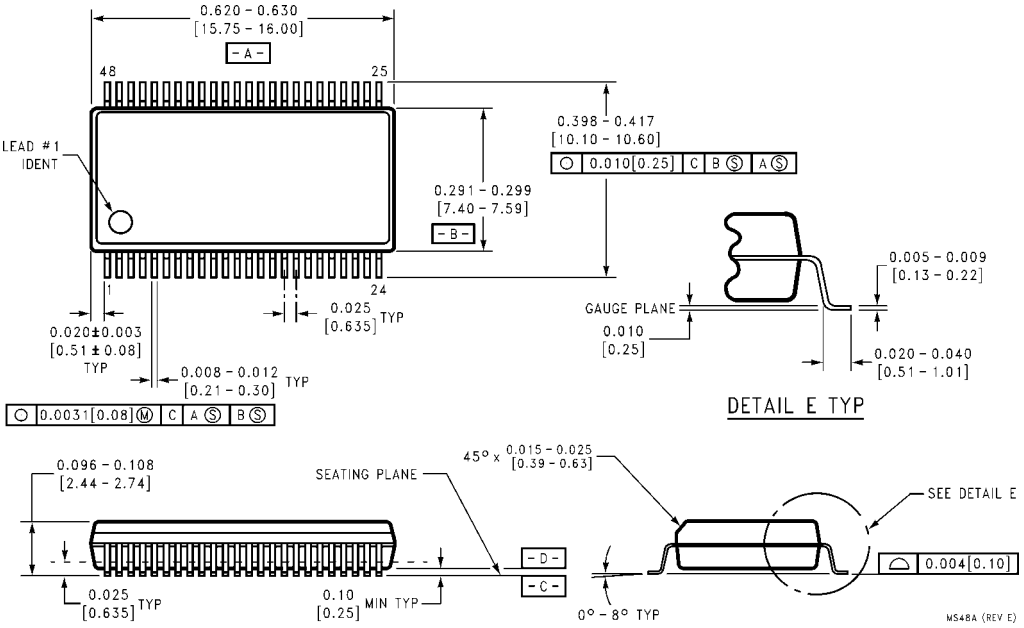
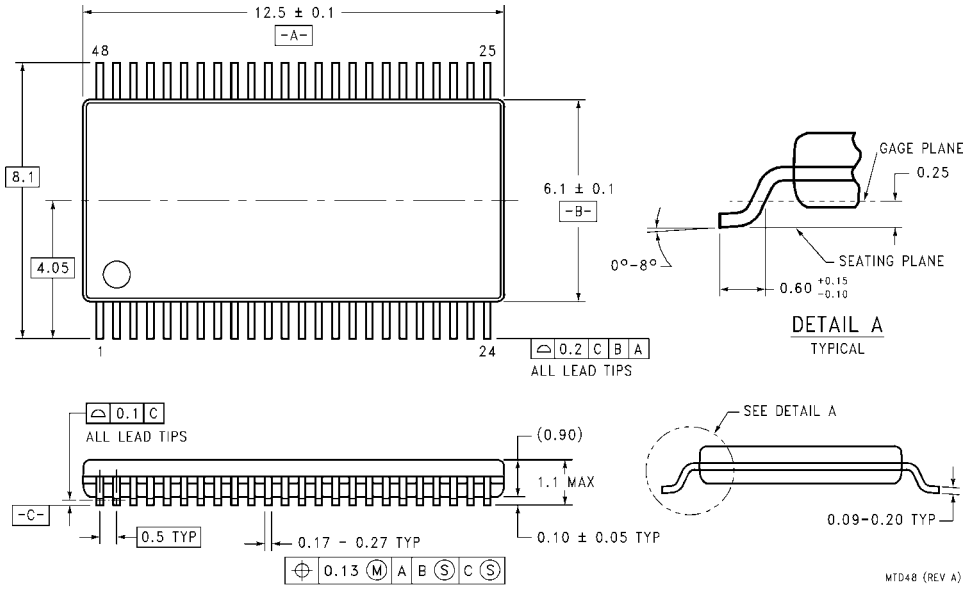


FIGURE 9. t_{PHZ} and t_{PLZ} Test Load and Waveforms DIR to B_1–B_8

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS48A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

June 1999
Revised June 1999

74LVX161284A
Low Voltage IEEE 161284 Translating Transceiver

General Description

The LVX161284A contains eight bidirectional data buffers and eleven control/status buffers to implement a full IEEE 1284 compliant interface. The device supports the IEEE 1284 standard, with the exception of output slew rate, and is intended to be used in an Extended Capabilities Port mode (ECP). The pinout allows for easy connection from the Peripheral (A-side) to the Host (cable side).

Outputs on the cable side can be configured to be either open drain or high drive (± 14 mA) and are connected to a separate power supply pin (V_{CC}—cable) to allow these outputs to be driven by a higher supply voltage than the A-side. The pull-up and pull-down series termination resistance of these outputs on the cable side is optimized to drive an external cable. In addition, all inputs (except HLH) and outputs on the cable side contain internal pull-up resistors connected to the V_{CC}—cable supply to provide proper termination and pull-ups for open drain mode.

Outputs on the Peripheral side are standard low-drive CMOS outputs designed to interface with 3V logic. The DIR input controls data flow on the A_1–A_8/B_1–B_8 transceiver pins.

Features

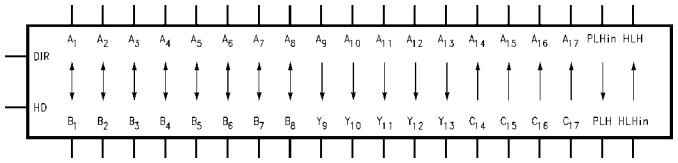
- Supports IEEE 1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals with the exception of output slew rate
- Translation capability allows outputs on the cable side to interface with 5V signals
- All inputs have hysteresis to provide noise margin
- B and Y output resistance optimized to drive external cable
- B and Y outputs in high impedance mode during power down
- Inputs and outputs on cable side have internal pull-up resistors
- Flow-through pin configuration allows easy interface between the “Peripheral and Host”
- Replaces the function of two (2) 74ACT1284 devices

Ordering Code

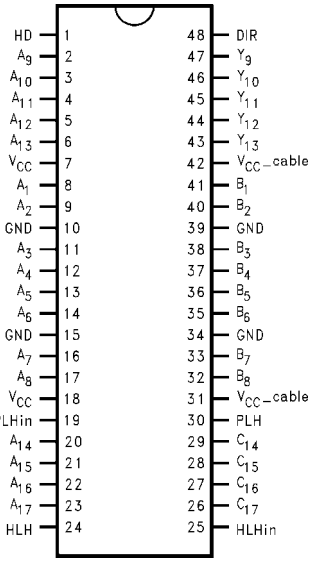
Order Number	Package Number	Package Description
74LVX161284AMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
HD	High Drive Enable Input (Active High)
DIR	Direction Control Input
A_1–A_8	Inputs or Outputs
B_1–B_8	Inputs or Outputs
A_9–A_{13}	Inputs
Y_9–Y_{13}	Outputs
A_{14}–A_{17}	Outputs
C_{14}–C_{17}	Inputs
PLH_{IN}	Peripheral Logic High Input
PLH	Peripheral Logic High Output
HLH_{IN}	Host Logic High Input
HLH	Host Logic High Output

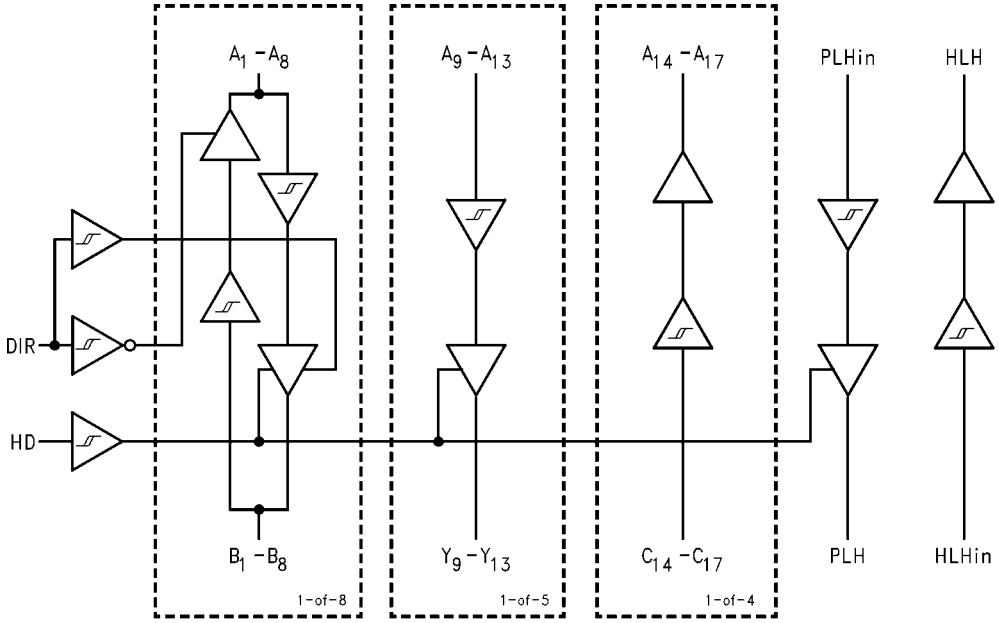
Truth Table

Inputs		Outputs
DIR	HD	
L	L	B_1–B_8 Data to A_1–A_8, and
		A_9–A_{13} Data to Y_9–Y_{13} (Note 1)
		C_{14}–C_{17} Data to A_{14}–A_{17}
		PLH Open Drain Mode
L	H	B_1–B_8 Data to A_1–A_8, and
		A_9–A_{13} Data to Y_9–Y_{13}
		C_{14}–C_{17} Data to A_{14}–A_{17}
H	L	A_1–A_8 Data to B_1–B_8 (Note 2)
		A_9–A_{13} Data to Y_9–Y_{13} (Note 1)
		C_{14}–C_{17} Data to A_{14}–A_{17}
		PLH Open Drain Mode
H	H	A_1–A_8 Data to B_1–B_8
		A_9–A_{13} Data to Y_9–Y_{13}
		C_{14}–C_{17} Data to A_{14}–A_{17}

Note 1: Y_9–Y_{13} Open Drain Outputs

Note 2: B_1–B_8 Open Drain Outputs

Logic Diagram



Absolute Maximum Ratings (Note 3)

Supply Voltage
- V_{CC} −0.5V to +4.6V
- $V_{CC—Cable}$ −0.5V to +7.0V
- $V_{CC—Cable}$ Must Be ≥ V_{CC}

Input Voltage (V_I)—(Note 4)
- A_1–A_{13}, PLH_{IN}, DIR, HD −0.5V to V_{CC} + 0.5V
- B_1–B_8, C_{14}–C_{17}, HLH_{IN} −0.5V to +5.5V (DC)
- B_1–B_8, C_{14}–C_{17}, HLH_{IN} −2.0V to +7.0V*

*40 ns Transient

Output Voltage (V_O)
- A_1–A_8, A_{14}–A_{17}, HLH −0.5V to V_{CC} +0.5V
- B_1–B_8, Y_9–Y_{13}, PLH −0.5V to +5.5V (DC)
- B_1–B_8, Y_9–Y_{13}, PLH −2.0V to +7.0V*

*40 ns Transient

DC Output Current (I_O)
- A_1–A_8, HLH ±25 mA
- B_1–B_8, Y_9–Y_{13} ±50 mA
- PLH (Output LOW) 84 mA
- PLH (Output HIGH) −50 mA

Input Diode Current (I_{IK})—(Note 4)
- DIR, HD, A_9–A_{13}, PLH, HLH, C_{14}–C_{17} −20 mA

Output Diode Current (I_{OK})
- A_1–A_8, A_{14}–A_{17}, HLH ±50 mA
- B_1–B_8, Y_9–Y_{13}, PLH −50 mA

DC Continuous V_{CC} or Ground Current ±200 mA

Storage Temperature −65°C to +150°C

ESD (HBM) Last Passing Voltage 2000V

Recommended Operating Conditions

Supply Voltage
- V_{CC} 3.0V to 3.6V
- $V_{CC—Cable}$ 3.0V to 5.5V

DC Input Voltage (V_I) 0V to V_{CC}

Open Drain Voltage (V_O) 0V to 5.5V

Operating Temperature (T_A) −40°C to +85°C

Note 3: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	$V_{CC—Cable}$ (V)	T_A = −40°C to +85°C Guaranteed Limits	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		3.0	3.0	−1.2	V	I_I = −18 mA
V_{IH}	Minimum High Level Input Voltage	A_n, B_n, PLH_{IN}, DIR, HD	3.0–3.6	3.0–5.5	2.0	V	
		C_n	3.0–3.6	3.0–5.5	2.3		
		HLH_{IN}	3.0–3.6	3.0–5.5	2.6		
V_{IL}	Maximum Low Level Input Voltage	A_n, B_n, PLH_{IN}, DIR, HD	3.0–3.6	3.0–5.5	0.8	V	
		C_n	3.0–3.6	3.0–5.5	0.8		
		HLH_{IN}	3.0–3.6	3.0–5.5	1.6		
ΔV_T	Minimum Input Hysteresis	A_n, B_n, PLH_{IN}, DIR, HD	3.3	5.0	0.4	V	V_T^+–V_T^-
		C_n	3.3	5.0	0.8		V_T^+–V_T^-
		HLH_{IN}	3.3	5.0	0.2		V_T^+–V_T^-
V_{OH}	Minimum High Level Output Voltage	A_n, HLH	3.0	3.0	2.8	V	I_{OH} = −50 µA
			3.0	3.0	2.4		I_{OH} = −4 mA
		B_n, Y_n	3.0	3.0	2.0		I_{OH} = −14 mA
		B_n, Y_n	3.0	4.5	2.23		I_{OH} = −14 mA
		PLH	3.15	3.15	3.1		I_{OH} = −500 µA
V_{OL}	Maximum Low Level Output Voltage	A_n, HLH	3.0	3.0	0.2	V	I_{OL} = 50 µA
			3.0	3.0	0.4		I_{OL} = 4 mA
		B_n, Y_n	3.0	3.0	0.8		I_{OL} = 14 mA
		B_n, Y_n	3.0	4.5	0.77		I_{OL} = 14 mA
		PLH	3.0	3.0	0.95		I_{OL} = 84 mA
		PLH	3.0	4.5	0.9		I_{OL} = 84 mA
R_D	Maximum Output Impedance	B_1–B_8, Y_9–Y_{13}	3.3	3.3	60	Ω	(Note 5) (Note 7)
			3.3	5.0	55		
	Minimum Output Impedance	B_1–B_8, Y_9–Y_{13}	3.3	3.3	30		(Note 5) (Note 7)
			3.3	5.0	35		

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CC} (V)	$V_{CC—Cable}$ (V)	$T_A = -40°C$ to $+85°C$ Guaranteed Limits	Units	Conditions
R_P	Maximum Pull-Up Resistance	$B_1–B_8$, $Y_9–Y_{13}$,	3.3	3.3	1650	Ω	
		$C_{14}–C_{17}$	3.3	5.0	1650		
	Minimum Pull-Up Resistance	$B_1–B_8$, $Y_9–Y_{13}$	3.3	3.3	1150		
		$C_{14}–C_{17}$	3.3	5.0	1150		
I_{IH}	Maximum Input Current in High State	$A_9–A_{13}$, PLH_{IN}, HD, DIR, HLH_{IN}	3.6	3.6	1.0	µA	$V_I = 3.6V$
		$C_{14}–C_{17}$	3.6	3.6	50.0		$V_I = 3.6V$
		$C_{14}–C_{17}$	3.6	5.5	100		$V_I = 5.5V$
I_{IL}	Maximum Input Current in Low State	$A_9–A_{13}$, PLH_{IN}, HD, DIR, HLH_{IN}	3.6	3.6	−1.0	µA	$V_I = 0.0V$
		$C_{14}–C_{17}$	3.6	3.6	−3.5	mA	$V_I = 0.0V$
		$C_{14}–C_{17}$	3.6	5.5	−5.0	mA	$V_I = 0.0V$
I_{OZH}	Maximum Output Disable Current (High)	$A_1–A_8$	3.6	3.6	20	µA	$V_O = 3.6V$
		$B_1–B_8$	3.6	3.6	50	µA	$V_O = 3.6V$
		$B_1–B_8$	3.6	5.5	100	µA	$V_O = 5.5V$
I_{OZL}	Maximum Output Disable Current (Low)	$A_1–A_8$	3.6	3.6	−20	µA	$V_O = 0.0V$
		$B_1–B_8$	3.6	3.6	−3.5	mA	
		$B_1–B_8$	3.6	5.5	−5.0	mA	
I_{OFF}	Power Down Output Leakage	$B_1–B_8$, $Y_9–Y_{13}$, PLH	0.0	0.0	100	µA	$V_O = 5.5V$
I_{OFF}	Power Down Input Leakage	$C_{14}–C_{17}$, HLH_{IN}	0.0	0.0	100	µA	$V_I = 5.5V$
$I_{OFF—ICC}$	PowerDown Leakage to V_{CC}		0.0	0.0	250	µA	(Note 6)
$I_{OFF—ICC2}$	Power Down Leakage to $V_{CC—Cable}$		0.0	0.0	250	µA	(Note 6)
I_{CC}	Maximum Supply Current		3.6	3.6	45	mA	$V_I = V_{CC}$ or GND
			3.6	5.5	70		$V_I = V_{CC}$ or GND

Note 5: Output impedance is measured with the output active low and active high (HD = high).

Note 6: Power-down leakage to V_{CC} or $V_{CC—Cable}$ is tested by simultaneously forcing all pins on the cable-side ($B_1–B_8$, $Y_9–Y_{13}$, PLH, $C_{14}–C_{17}$ and HLH_{IN}) to 5.5V and measuring the resulting I_{CC} or $I_{CC—Cable}$.

Note 7: This parameter is guaranteed but not tested, characterized only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$ $V_{CC} = 3.0V–3.6V$ $V_{CC—Cable} = 4.5V–5.5V$		Units	Fig. No.
		Min	Max		
t_{PHL}	$A_1–A_8$ to $B_1–B_8$	1.0	8.5	ns	1
t_{PLH}	$A_1–A_8$ to $B_1–B_8$	1.0	8.5	ns	2
t_{PHL}	$B_1–B_8$ to $A_1–A_8$	1.0	14.0	ns	3
t_{PLH}	$B_1–B_8$ to $A_1–A_8$	1.0	14.0	ns	3
t_{PHL}	$A_9–A_{13}$ to $Y_9–Y_{13}$	1.0	8.5	ns	1
t_{PLH}	$A_9–A_{13}$ to $Y_9–Y_{13}$	1.0	8.5	ns	2
t_{PHL}	$C_{14}–C_{17}$ to $A_{14}–A_{17}$	1.0	10.0	ns	3
t_{PLH}	$C_{14}–C_{17}$ to $A_{14}–A_{17}$	1.0	10.0	ns	3
t_{SKEW}	LH-LH or HL-HL		2.0	ns	(Note 9)
t_{PHL}	PLH_{IN} to PLH	1.0	8.5	ns	1
t_{PLH}	PLH_{IN} to PLH	1.0	8.5	ns	2
t_{PHL}	HLH_{IN} to HLH	1.0	10.0	ns	3
t_{PLH}	HLH_{IN} to HLH	1.0	12.0	ns	3
t_{PHZ}	Output Disable Time	1.0	10.0	ns	7
t_{PLZ}	DIR to $A_1–A_8$	1.0	10.0		
t_{PZH}	Output Enable Time	1.0	10.0	ns	8
t_{PZL}	DIR to $A_1–A_8$	1.0	10.0		
t_{PHZ}	Output Disable Time	1.0	13.0	ns	9
t_{PLZ}	DIR to $B_1–B_8$	1.0	10.0		
t_{pEN}	Output Enable Time HD to $B_1–B_8$, $Y_9–Y_{13}$	1.0	8.0	ns	2
t_{pDIS}	Output Disable Time HD to $B_1–B_8$, $Y_9–Y_{13}$	1.0	12.0	ns	2

Note 8: Open Drain

Note 9: t_{SKEW} is measured for common edge output transitions and compares the measured propagation delay for a given path type:

(i) $A_1–A_8$ to $B_1–B_8$, $A_9–A_{13}$ to $Y_9–Y_{13}$

(ii) $B_1–B_8$ to $A_1–A_8$

(iii) $C_{14}–C_{17}$ to $A_{14}–A_{17}$

Note 10: Pulse Generator for all pulses; Rate ≤1.0 MHz; $Z_O \leq 50\Omega$; $t_f \leq 2.5$ ns, $t_r \leq 2.5$ ns.

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	3	pF	V_{CC} = 0.0V (HD, DIR, $A_9–A_{13}$, $C_{14}–C_{17}$, PLH_{IN} and HLH_{IN})
$C_{I/O}$ (Note 11)	I/O Pin Capacitance	5	pF	V_{CC} = 3.3V

Note 11: $C_{I/O}$ is measured at frequency = 1 MHz, per MIL-STD-883B, Method 3012

AC Loading and Waveforms

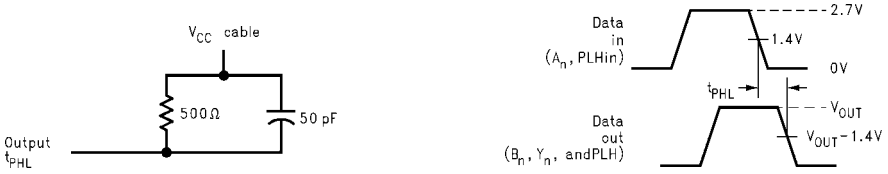


FIGURE 1. t_{PHL} Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}
PLHin to PLH

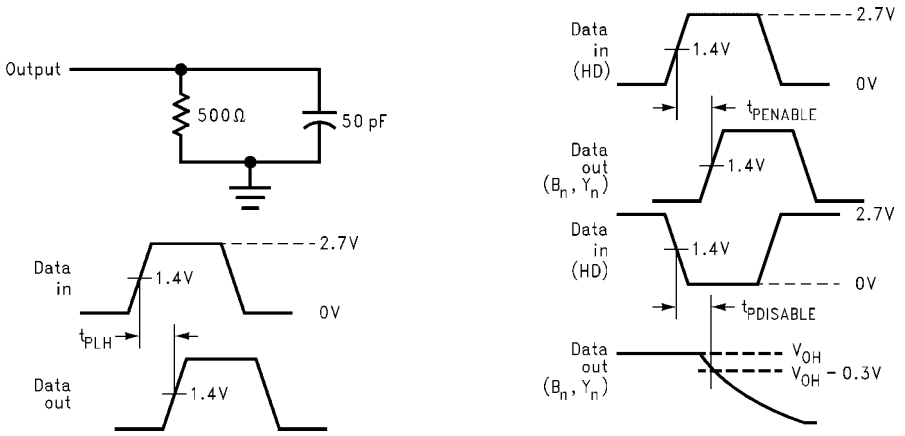


FIGURE 2. t_{PLH}, t_{pEn}, t_{pDis} Test Load and Waveforms
A_1–A_8 to B_1–B_8, A_9–A_{13} to Y_9–Y_{13}
PLHin to PLH, HD to B_1–B_8, Y_9–Y_{13}, PLH

V_{MO} = 50% V_{CC}

FIGURE 3. t_{PHL}, t_{PLH} Test Load and Waveforms
B_1–B_8 to A_1–A_8, C_{14}–C_{17} to A_{14}–A_{17}, HLHin to HLH

AC Loading and Waveforms (Continued)

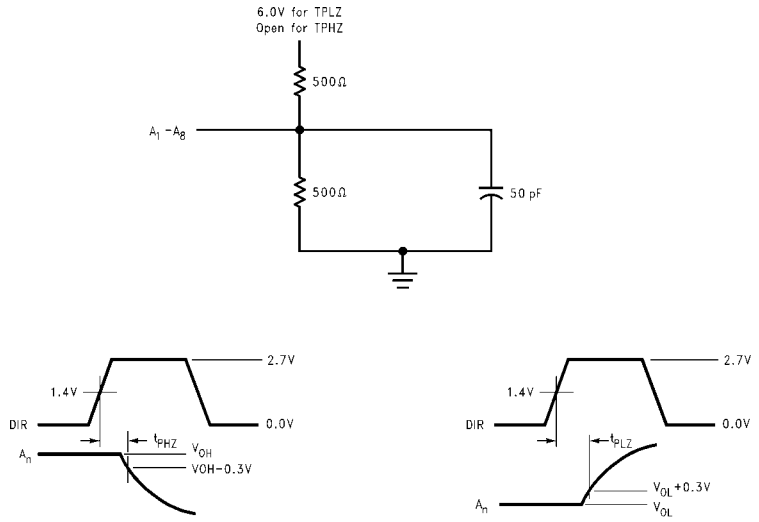


FIGURE 4. t_{PHZ} and t_{PLZ} Test Load and Waveforms, DIR to A_1–A_8

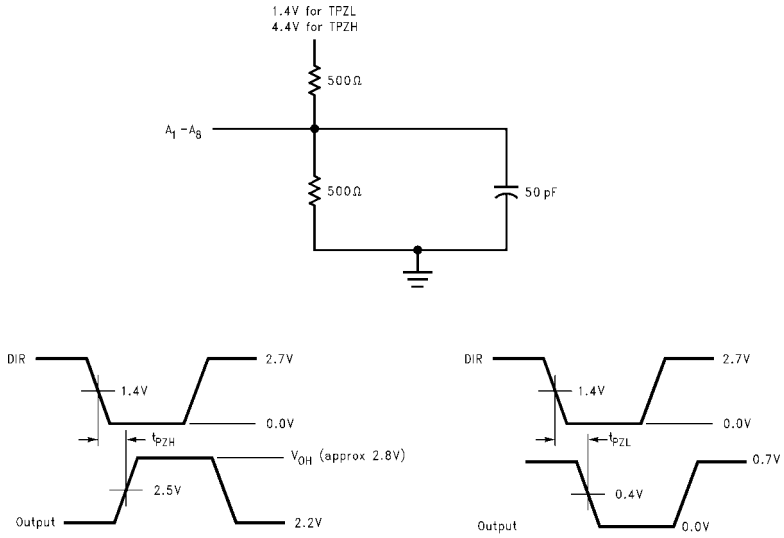


FIGURE 5. t_{PZH} and t_{PZL} Test Load and Waveforms, DIR to A_1–A_8

AC Loading and Waveforms (Continued)

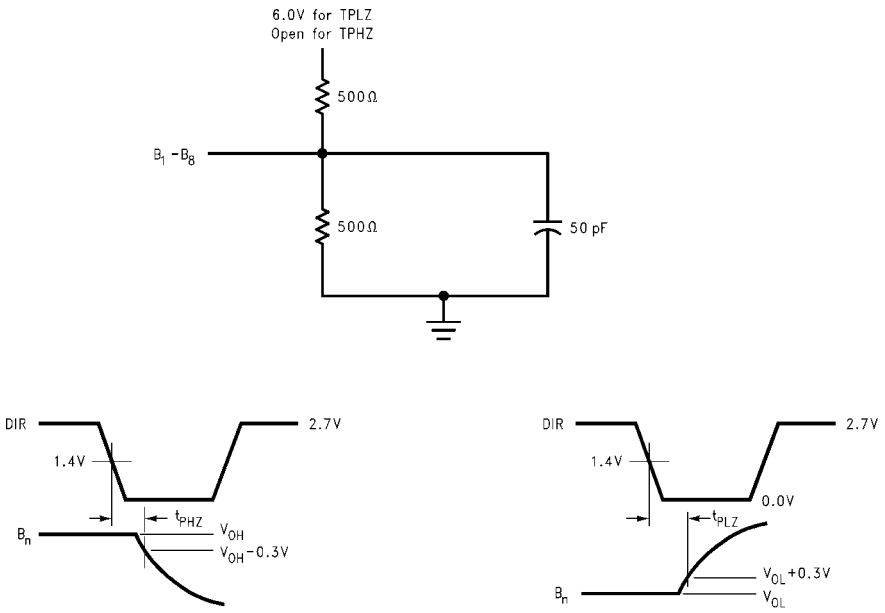
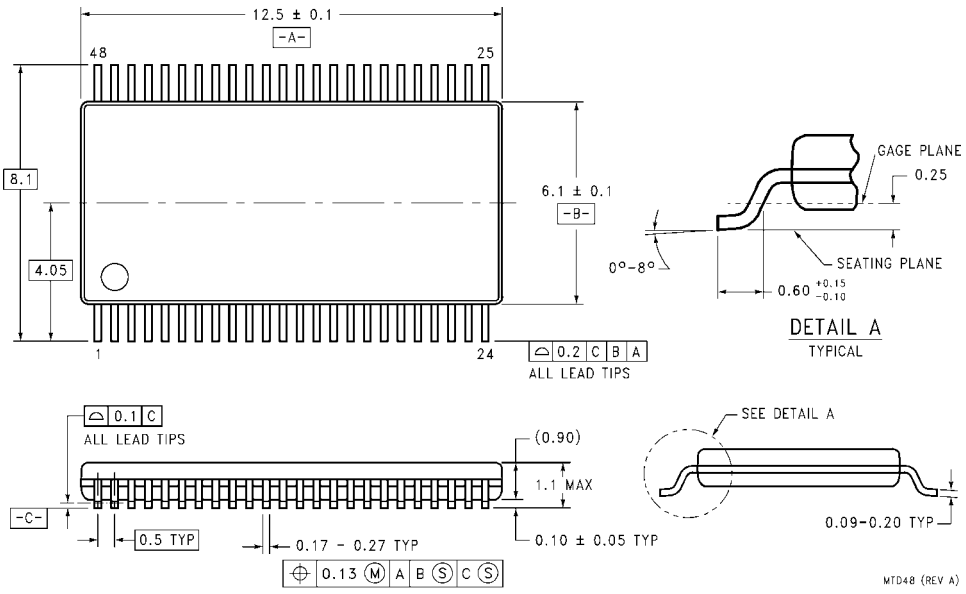


FIGURE 6. t_{PHZ} and t_{PLZ} Test Load and Waveforms
DIR to B_1–B_8

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

National Semiconductor

ADVANCE INFORMATION
February 1996

74LVX16212
24-Bit Bus-Exchange Switch

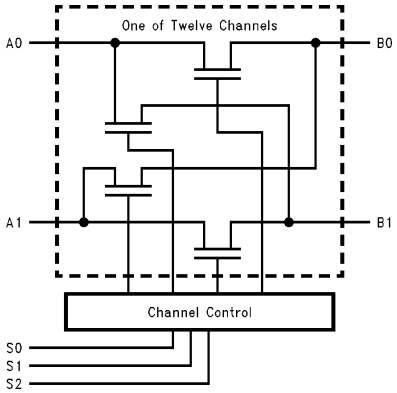
General Description

The LVX16212 provides 24 bits of high-speed CMOS TTL-compatible bus switches or bus exchangers. The low on resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise. The device provides data exchanging between the four signal ports (A0 B0, A1 and B1) through the data-select (S0, S1 and S2) inputs.

Features

- 5Ω switch connection between two ports
- Zero propagation delay
- Zero ground bounce in flow-through mode
- Control inputs compatible with TTL level
- Available in SSOP and TSSOP

Logic Symbol



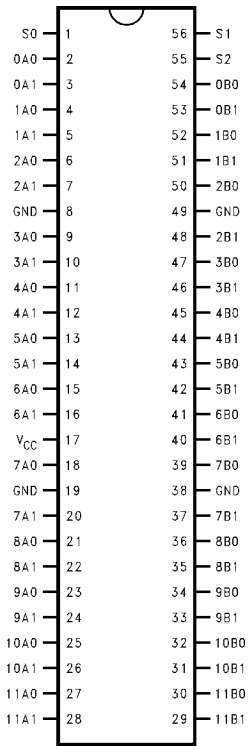
TL/F/12641–1

Truth Table

S2	S1	S0	A0	A1	Function
L	L	L	Z	Z	Disconnect
L	L	H	B0	Z	A0 to B0
L	H	L	B1	Z	A0 to B1
L	H	H	Z	B0	A1 to B0
H	L	L	Z	B1	A1 to B1
H	L	H	Z	Z	Disconnect
H	H	L	B0	B1	A0 to B0, A1 to B1
H	H	H	B1	B0	A0 to B1, A1 to B0

Connection Diagram

Pin Assignment for SSOP and TSSOP



TL/F/12641–2

	SSOP	TSSOP
Order Number	74LVX16212MEA 74LVX16212MEAX	74LVX16212MTD 74LVX16212MTDX
See NS Package Number	MS56A	MTD56

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Switch Voltage (V_S)	−0.5 to +7.0V
DC Input Input Voltage (V_I) (Note 2)	−0.5 to +7.0V
DC Input Diode Current with ($V_I < 0$)	−20 mA
DC Output (I_O) Sink Current	120 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation	0.5W

Note 1: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Note 2: *The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.*

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.0V to 5.5V
Free Air Operating Temperature (T_A)	−40°C to +85°C

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	74LVX16212 $T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 5)	Max		
V_{IK}	Maximum Clamp Diode Voltage	4.75			−1.2	V	$I_{IN} = -18$ mA
V_{IH}	Minimum High Level Input Voltage	4.75–5.25	2.0			V	
V_{IL}	Maximum Low Level Input Voltage	4.75–5.25			0.8	V	
I_{IN}	Maximum Input Leakage Current	0			10	μA	$0 \le V_{IN} \le 5.25V$
		5.25			±1	μA	$0 \le V_{IN} \le 5.25V$
I_{OZ}	Maximum TRI-STATE® I/O Leakage	5.25			±10	μA	$0 \le A, B \le V_{CC}$
I_{OS}	Short Circuit Current	4.75	100			mA	$V_I(A), V_I(B) = 0V$, $V_I(B), V_I(A) = 4.75V$
R_{ON}	Switch On Resistance (Note 3)	4.75		5	7	Ω	$V_I = 0V$, $I_{ON} = 30$ mA
				10	15	Ω	$V_I = 2.4V$, $I_{ON} = 15$ mA
I_{CC}	Maximum Quiescent Supply Current	5.25		0.2	20	μA	$V_I = V_{CC}$, GND $I_O = 0$
ΔI_{CC}	Increase in I_{CC} per Input (Note 4)	5.25			2.5	mA	$V_{IN} = 3.15V$, $I_O = 0$ per Control Input

Note 3: Measured by voltage drop between A and B pin at indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 4: Per TTL driven Input ($V_{IN} = 3.15V$, control inputs only). A and B pins do not contribute to I_{CC}.

Note 5: All typical values are at $V_{CC} = 5.0V$, $T_A = 25°C$.

AC Electrical Characteristics:

Symbol	Parameter	V_{CC} (V)	74LVX16212 $T_A = -40°C$ to $+85°C$ $C_L = 50$ pF			Units
			Min	Typ (Note 5)	Max	
T_{PLH} T_{PHL}	Data Propagation Delay An to Bn or Bn to An (Note 6)	4.75			0.25	ns
T_{PLH} T_{PHL}	Switch Exchange Time S0, S1, S2 to An or Bn	4.75	1.5		6.5	ns
T_{PZL} T_{PZH}	Switch Enable Time S0, S1, S2 to An, Bn	4.75	1.5		6.5	ns
T_{PLZ} T_{PHZ}	Switch Disable Time S0, S1, S2 to An, Bn	4.75	1.5		5.5	ns

Note 5: All typical values are at $V_{CC} = 5.0V$, $T_A = 25°C$.

Note 6: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On resistance of the switch and the load capacitance. The time constant for the switch and alone is of the order of 0.25 ns for 50 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

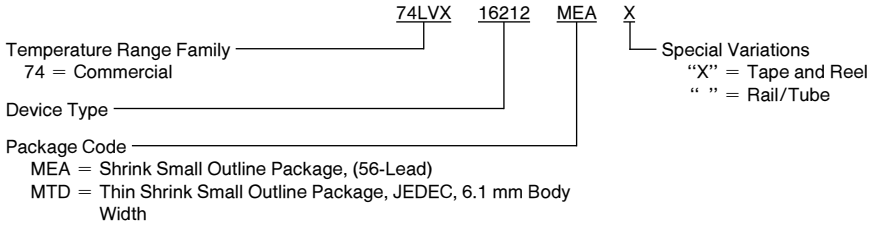
Capacitance (Note)

Symbol	Parameter	Typ	Max	Units	Conditions
C_{IN}	Control Input Capacitance	4	6	pF	$V_{CC} = 5.0V$
$C_{I/O}$ (OFF)	Input/Output Capacitance	9	13	pF	$V_{CC} = 5.0V$

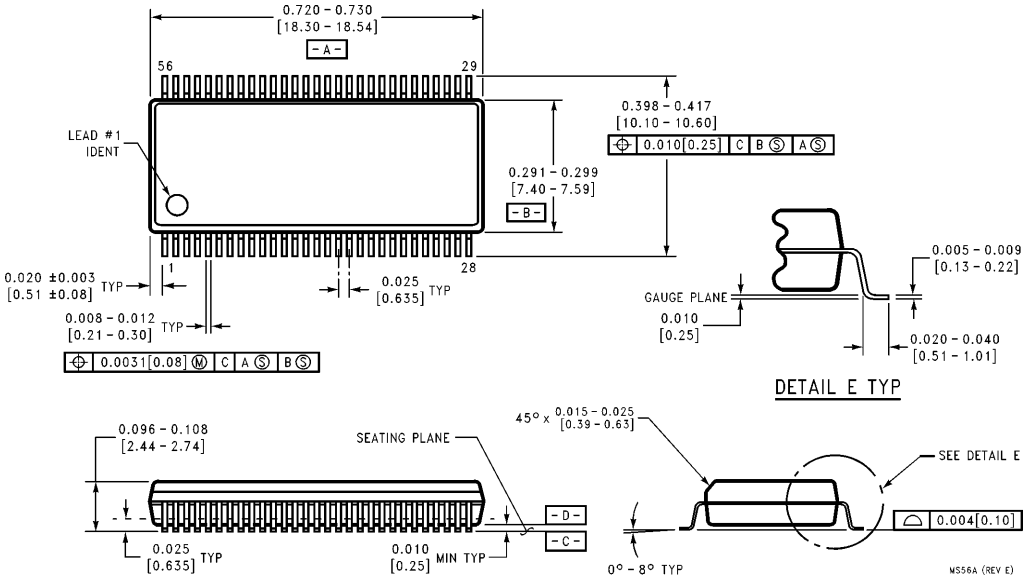
Note: Capacitance is characterized but not tested.

74LVX16212 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

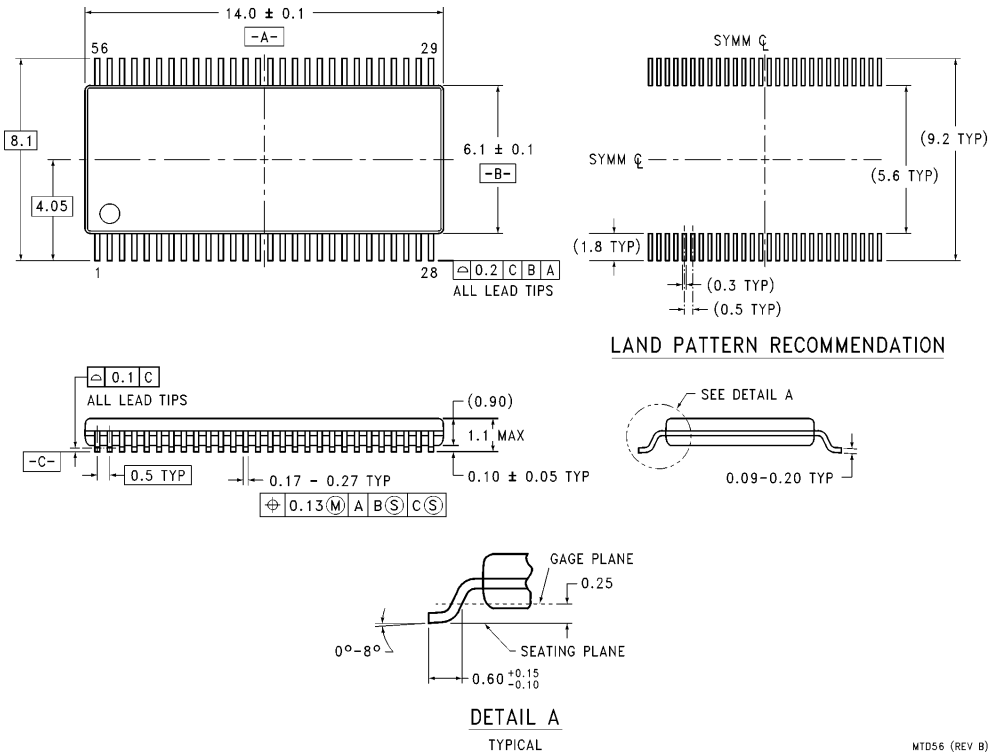


Physical Dimensions All dimensions are in inches (millimeters)



56-Lead (0.300" Wide) Molded Shrink Small Outline Package
Order Number 74LVX16212MEA or 74LVX16212MEAX
NS Package Number MS56A

Physical Dimensions All dimensions are in millimeters (Continued)



56-Lead Molded Thin Shrink Small Outline Package, JEDEC, 6.1 mm Body Width
Order Number 74LVX16212MTD or 74LVX16212MTDX
NS Package Number MTD56

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1996
Revised March 1999

74LVX163
Low Voltage Synchronous Binary Counter with Synchronous Clear

General Description

The LVX163 is a synchronous modulo-16 binary counter. This device is synchronously presettable for application in programmable dividers and has two types of Count Enable inputs plus a Terminal Count output for versatility in forming multistage counters. The CLK input is active on the rising edge. Both $\overline{PE}$ and $\overline{MR}$ inputs are active on low logic levels. Presetting is synchronous to rising edge of the CLK and the Clear function of the LVX163 is synchronous to the CLK. Two enable inputs (CEP and CET) and Carry Output are provided to enable easy cascading of counters, which facilitates easy implementation of n-bit counters without using external gates.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

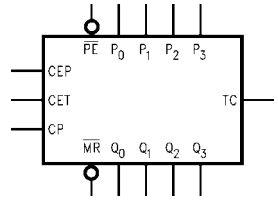
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise and dynamic threshold performance

Ordering Code:

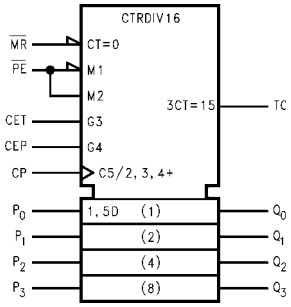
Order Number	Package Number	Package Description
74LVX163M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow
74LVX163SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX163MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

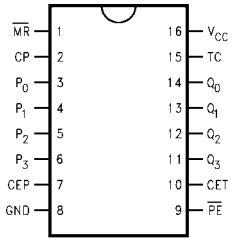
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
CEP	Count Enable Parallel Input
CET	Count Enable Trickle Input
CP	Clock Pulse Input
$\overline{MR}$	Synchronous Master Reset Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Inputs
Q_0–Q_3	Flip-Flop Outputs
TC	Terminal Count Output

Functional Description

The LVX163 counts in modulo-16 binary sequence. From state 15 (HHHH) it increments to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: synchronous reset, parallel load, count-up and hold. Four control inputs—Synchronous Reset ($\overline{MR}$), Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides counting and parallel loading and allows all outputs to go LOW on the next rising edge of CP. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{MR}$ HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The LVX163 uses D-type edge-triggered flip-flops and changing the $\overline{MR}$, $\overline{PE}$, CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 15. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to $\overline{TC}$ delay of the first stage, plus the cumulative $\overline{CET}$ to $\overline{TC}$ delays of the intermediate stages, plus the $\overline{CET}$ to CP setup time of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in *Figure 2* are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle takes 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to $\overline{TC}$ delay of the first stage plus the $\overline{CEP}$ to CP setup time of the last stage. The $\overline{TC}$ output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters. When the Parallel Enable ($\overline{PE}$) is LOW, the parallel data outputs O_0–O_3 are active and follow the flip-flop Q outputs. A HIGH signal on $\overline{PE}$ forces O_0–O_3 to the High impedance state but does not prevent counting, loading or resetting.

Logic Equations: Count Enable = CEP • CET • $\overline{PE}$

$TC = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet CET$

Mode Select Table

$\overline{MR}$	$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (⌐)
L	X	X	X	Reset (Clear)
H	L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	H	Count (Increment)
H	H	L	X	No Change (Hold)
H	H	X	L	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

State Diagram

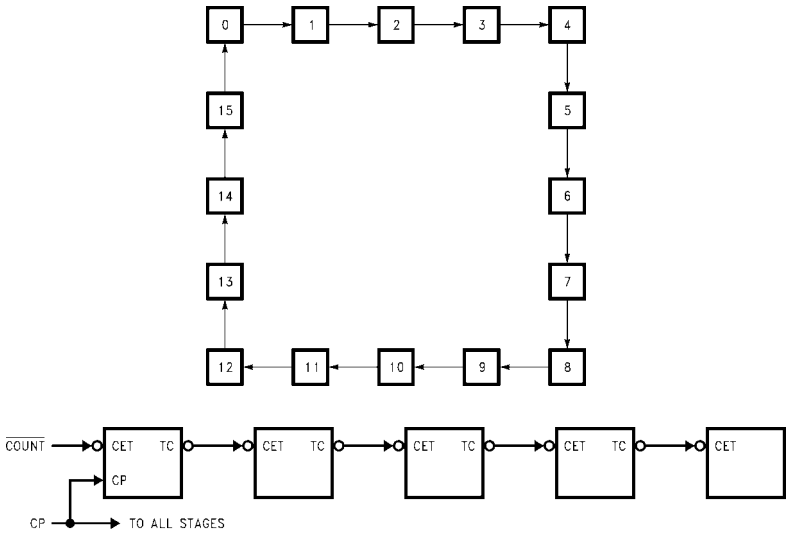


FIGURE 1.

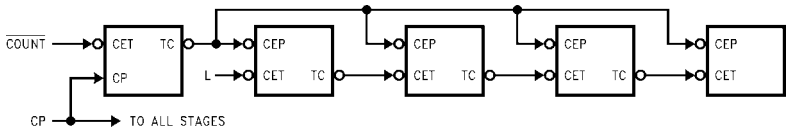
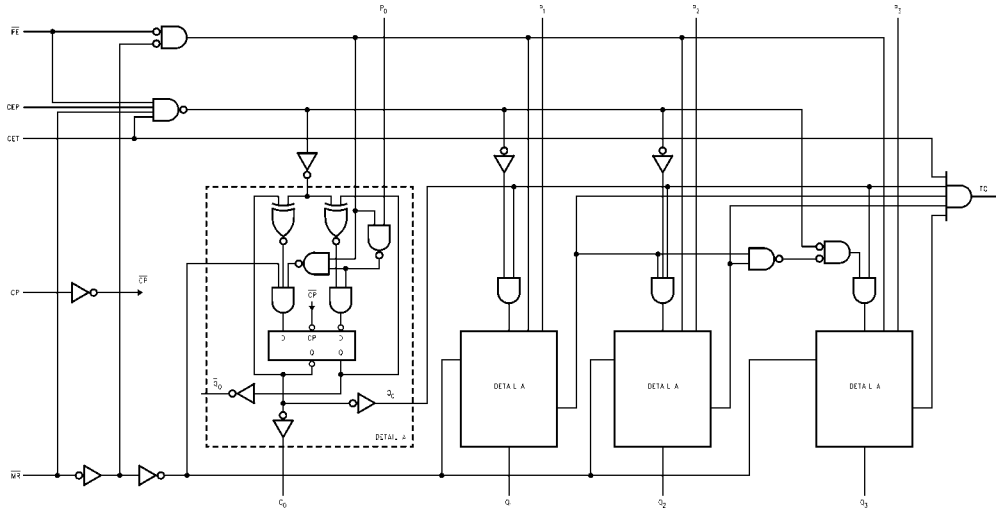


FIGURE 2.

Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/Δv)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.5			1.5		V		
		3.0	2.0			2.0				
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5	V		
		3.0			0.8		0.8			
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	3.3	0.2	0.5	V	50
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.2	−0.5	V	50
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	2.7		9.0	14.0	1.0	16.0	ns	$C_L = 15$ pF
t_{PHL}	Time (CP–Q_n)			11.3	17.0	1.0	19.0		$C_L = 50$ pF
		3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	$C_L = 15$ pF
				10.8	16.3	1.0	18.5		$C_L = 50$ pF
t_{PLH}	Propagation Delay	2.7		9.5	14.3	1.0	16.7	ns	$C_L = 15$ pF
t_{PHL}	Time (CP–TC, Count)			12.5	18.5	1.0	20.5		$C_L = 50$ pF
		3.3 ± 0.3		8.7	13.6	1.0	16.0	ns	$C_L = 15$ pF
				11.2	17.1	1.0	19.5		$C_L = 50$ pF
t_{PLH}	Propagation Delay	2.7		11.4	18.0	1.0	21.0	ns	$C_L = 15$ pF
t_{PHL}	Time (CP–TC, Load)			14.0	21.0	1.0	24.0		$C_L = 50$ pF
		3.3 ± 0.3		11.0	17.2	1.0	20.0	ns	$C_L = 15$ pF
				13.5	20.7	1.0	23.5		$C_L = 50$ pF
t_{PLH}	Propagation Delay	2.7		8.6	13.5	1.0	15.0	ns	$C_L = 15$ pF
t_{PHL}	Time (CET–TC)			11.0	16.5	1.0	18.5		$C_L = 50$ pF
		3.3 ± 0.3		7.5	12.3	1.0	14.5	ns	$C_L = 15$ pF
				10.5	15.8	1.0	18.0		$C_L = 50$ pF
f_{MAX}	Maximum Clock	2.7	75	115		65		MHz	$C_L = 15$ pF
	Frequency		50	80		45			$C_L = 50$ pF
		3.3 ± 0.3	80	130		70		MHz	$C_L = 15$ pF
			55	85		50			$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			23				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

When the outputs drive a capacitive load, total current consumption is the sum of C_{PD}, and ΔI_{CC} which is obtained from the following formula:

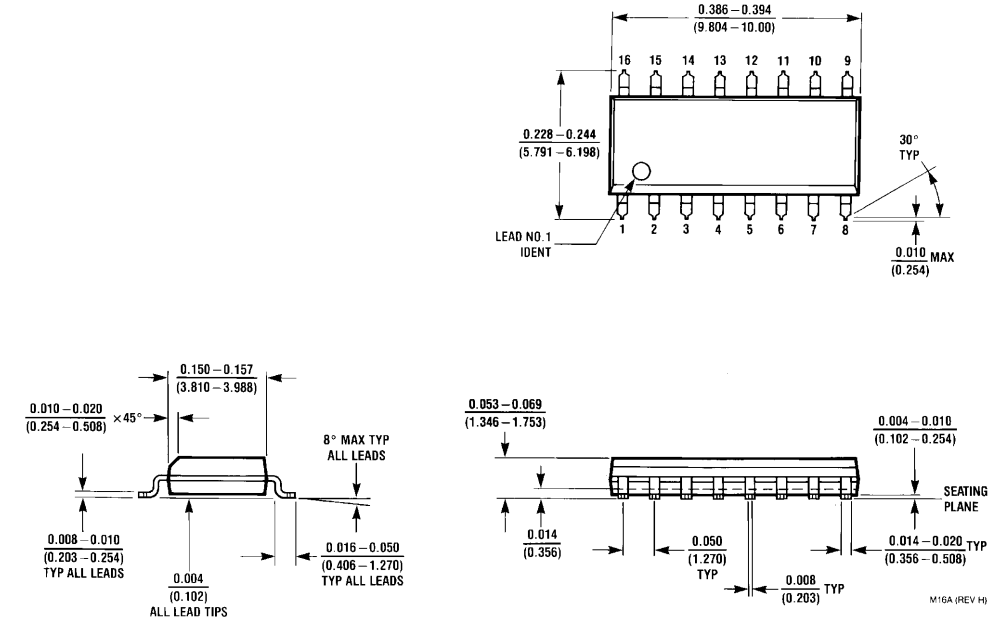
$$\Delta I_{CC} = F_{CP} \bullet V_{CC} \left(\frac{C_{QO}}{2} + \frac{C_{Q1}}{4} + \frac{C_{Q2}}{8} + \frac{C_{Q3}}{16} + \frac{C_{TC}}{16} \right)$$

C_{Q0}–C_{Q3} and C_{TC} are the capacitances at Q0–Q3 and TC, respectively. F_{CP} is the input frequency of the CP.

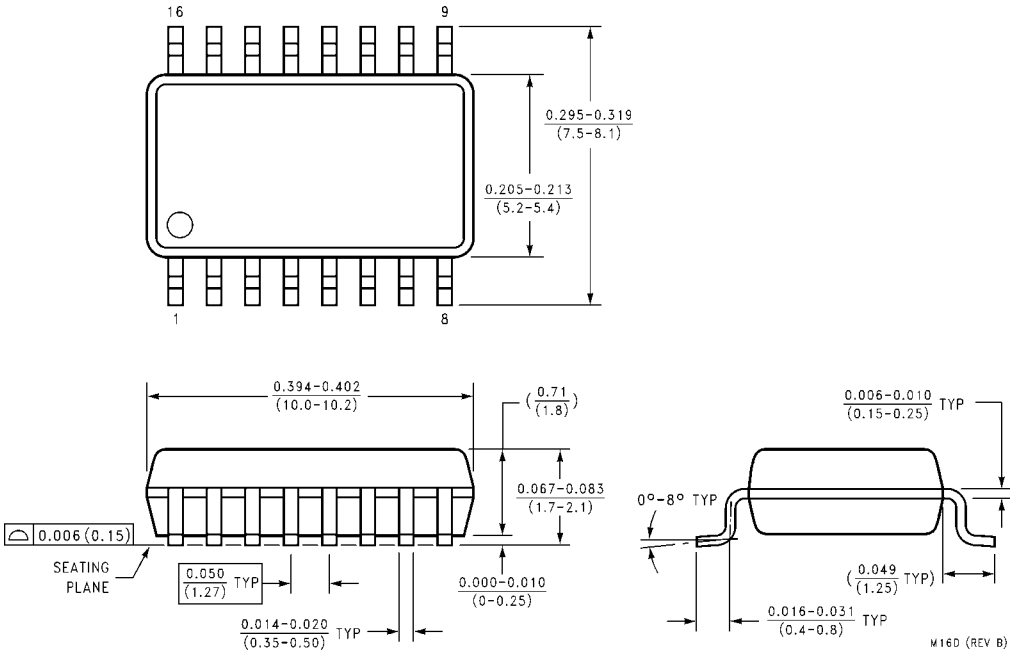
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$	Units
			Guaranteed Minimum		
t_S	Minimum Setup Time	2.7	5.5	6.5	ns
	(P_n–CP)	3.3 ± 0.3	5.5	6.5	
t_S	Minimum Setup Time	2.7	8.0	9.5	ns
	($\overline{PE}$ –CP)	3.3 ± 0.3	8.0	9.5	
t_S	Minimum Setup Time	2.7	7.5	9.0	ns
	(CEP or CET–CP)	3.3 ± 0.3	7.5	9.0	
t_S	Minimum Setup Time	2.7	4.0	4.0	ns
	($\overline{MR}$ –CP)	3.3 ± 0.3	4.0	4.0	
t_H	Minimum Hold Time	2.7	1.0	1.0	ns
	(P_n–CP)	3.3 ± 0.3	1.0	1.0	
t_H	Minimum Hold Time	2.7	1.0	1.0	ns
	($\overline{PE}$ –CP)	3.3 ± 0.3	1.0	1.0	
t_H	Minimum Hold Time	2.7	1.0	1.0	ns
	(CEP or CET–CP)	3.3 ± 0.3	1.0	1.0	
t_H	Minimum Hold Time	2.7	1.5	1.5	ns
	($\overline{MR}$ –CP)	3.3 ± 0.3	1.5	1.5	
$t_W(L)$	Minimum Pulse Width	2.7	5.0	5.0	ns
$t_W(H)$	CP (Count)	3.3 ± 0.3	5.0	5.0	

Physical Dimensions inches (millimeters) unless otherwise noted

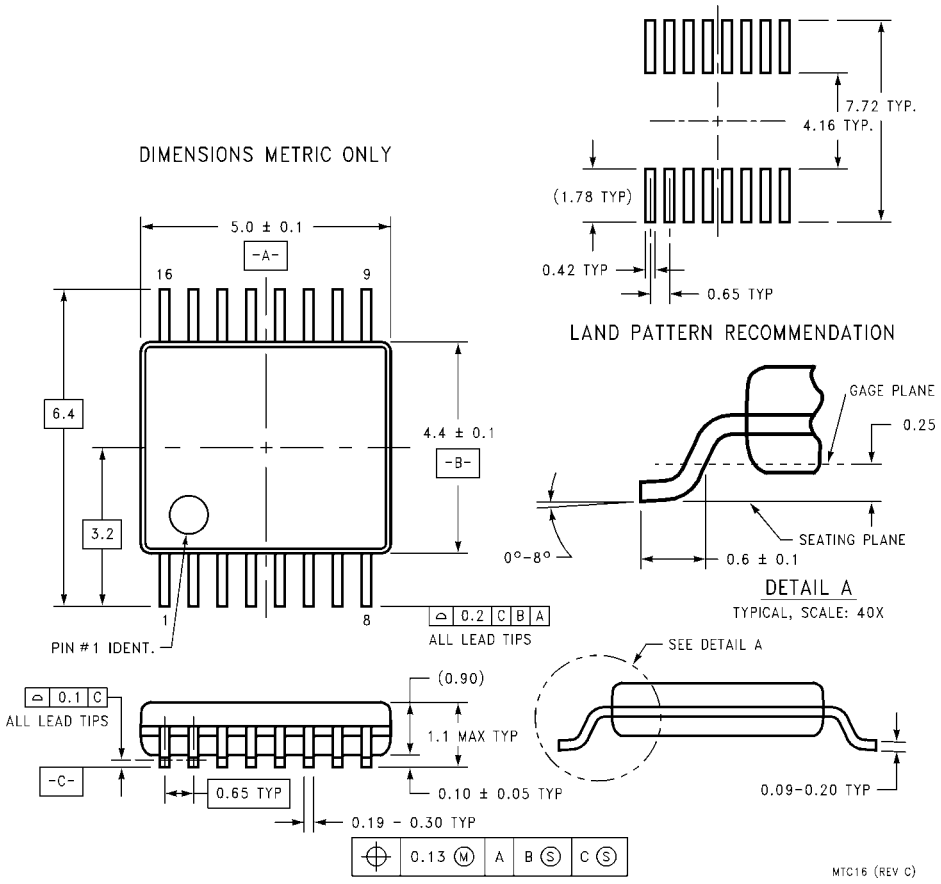


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX174
Low Voltage Hex D-Type Flip-Flop with Master Reset

General Description

The LVX174 is a high-speed hex D flip-flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the LOW-to-HIGH clock transition. The device has a Master Reset to simultaneously clear all flip-flops.

Features

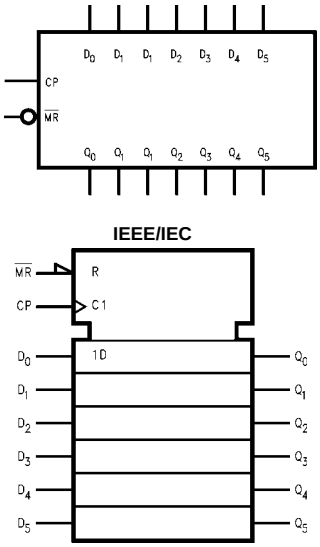
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

Order Number	Package Number	Package Description
74LVX174M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX174SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX174MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

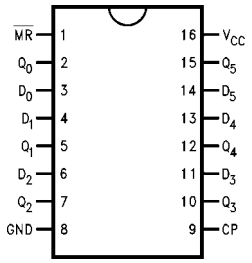
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



IEEE/IEC

Connection Diagram



Pin Descriptions

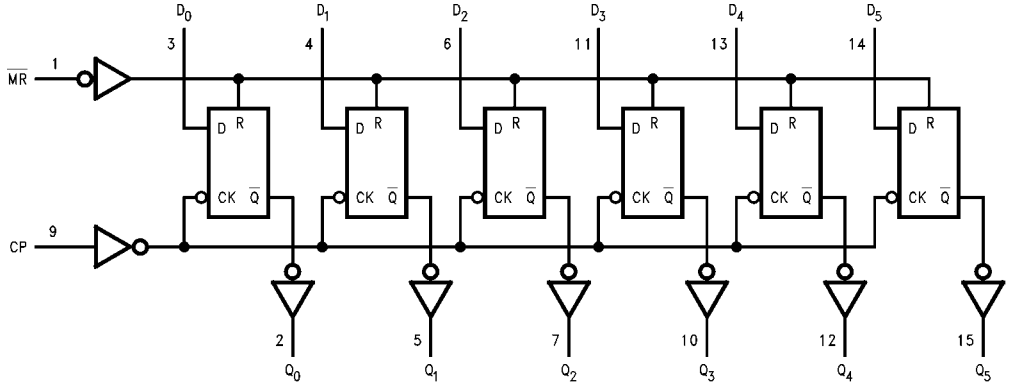
Pin Names	Description
D_0–D_5	Data Inputs
CP	Clock Pulse Input
$\overline{MR}$	Master Reset Input
Q_0–Q_5	Outputs

Truth Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load '1'	H	⌐	H	H
Load '0'	H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: (Input t_r = t_f = 3 ns)

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		7.6	14.5	1.0	17.5	ns	15
t_{PHL}	Delay Time			10.1	18.0	1.0	21.0		50
	CP to Q_n	3.3 ± 0.3		5.9	9.3	1.0	11.0		15
				8.4	12.8	1.0	14.5		50
t_{PHL}	Propagation Delay	2.7		7.9	15.0	1.0	18.5	ns	15
	$\overline{MR}$ to Q_n			10.4	18.5	1.0	22.0		50
		3.3 ± 0.3		6.2	9.7	1.0	11.5		15
				8.7	13.2	1.0	15.0		50
t_S	Setup Time	2.7	7.5			8.5		ns	
	D_n to CP	3.3 ± 0.3	5.0			6.0			
t_H	Hold Time	2.7	0			0			
	D_n to CP	3.3 ± 0.3	0			0			
t_{REC}	Removal Time	2.7	4.5			4.5		ns	
	$\overline{MR}$ to CP	3.3 ± 0.3	3.0			3.0			
t_W	Clock Pulse	2.7	6.5			7.5			
	Width	3.3 ± 0.3	5.0			5.0			
t_W	$\overline{MR}$ Pulse	2.7	6.5			7.5		ns	
	Width	3.3 ± 0.3	5.0			5.0			
f_{MAX}	Maximum Clock	2.7	65	130		55		MHz	15
	Frequency		45	60		40			50
		3.3 ± 0.3	115	180		95			15
			65	95		55			50
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

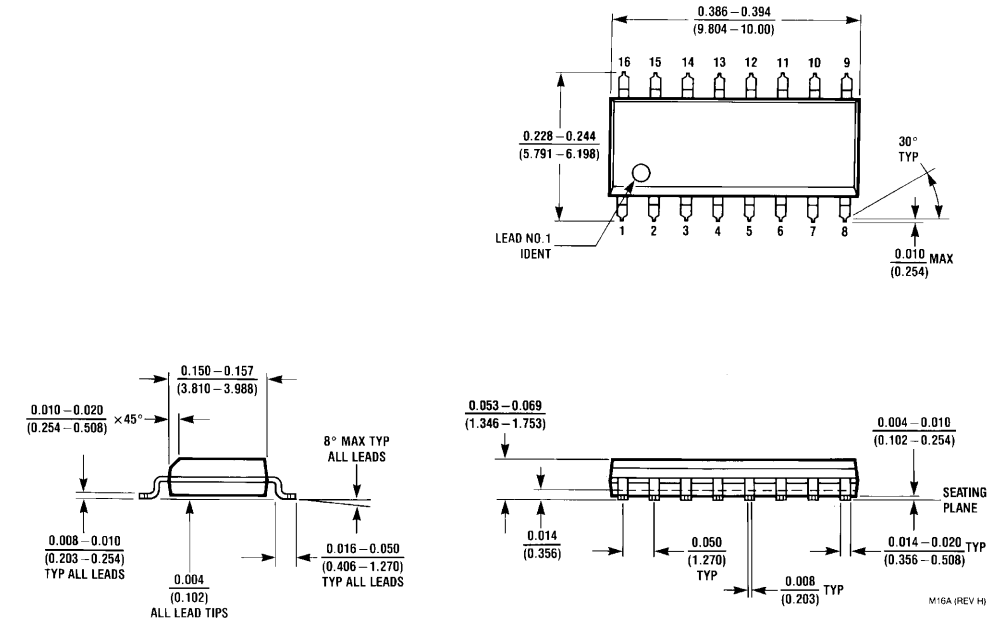
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		29				pF

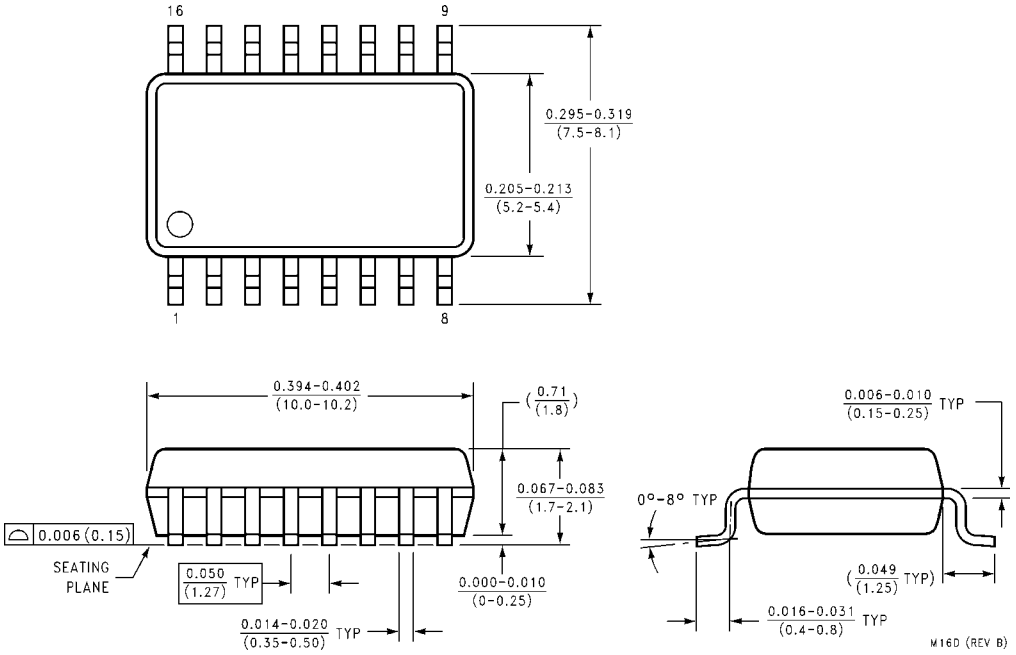
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per F/F)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

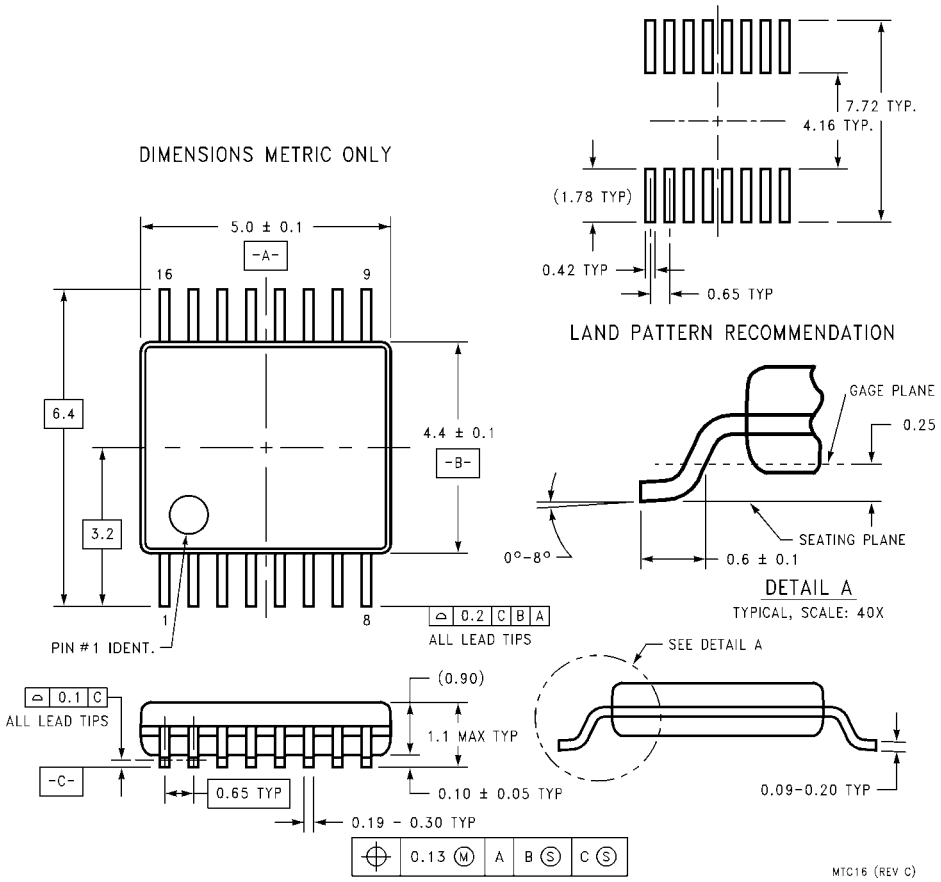


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX240
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVX240 is an octal inverting buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

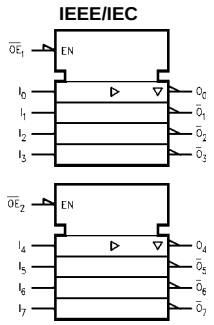
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

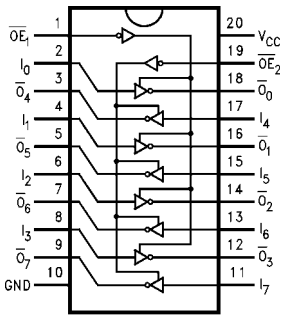
Order Number	Package Number	Package Description
74LVX240M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-130, 0.300" Wide
74LVX240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: Absolute Maximum Ratings are those values beyond which the safety to the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output	3.6			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: (Input t_r = t_f = 3 ns)

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		5.7	10.1	1.0	12.5	ns	$C_L = 15$ pF
t_{PHL}	Delay Time			8.2	13.6	1.0	16.0		$C_L = 50$ pF
		3.3 ± 0.3		4.3	6.2	1.0	7.5		$C_L = 15$ pF
				6.8	9.7	1.0	11.0		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		7.1	13.8	1.0	16.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			9.6	17.3	1.0	20.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		5.5	8.8	1.0	10.5		$C_L = 15$ pF, $R_L = 1$ kΩ
				8.0	12.3	1.0	14.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		11.6	16.0	1.0	19.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		9.7	11.4	1.0	13.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

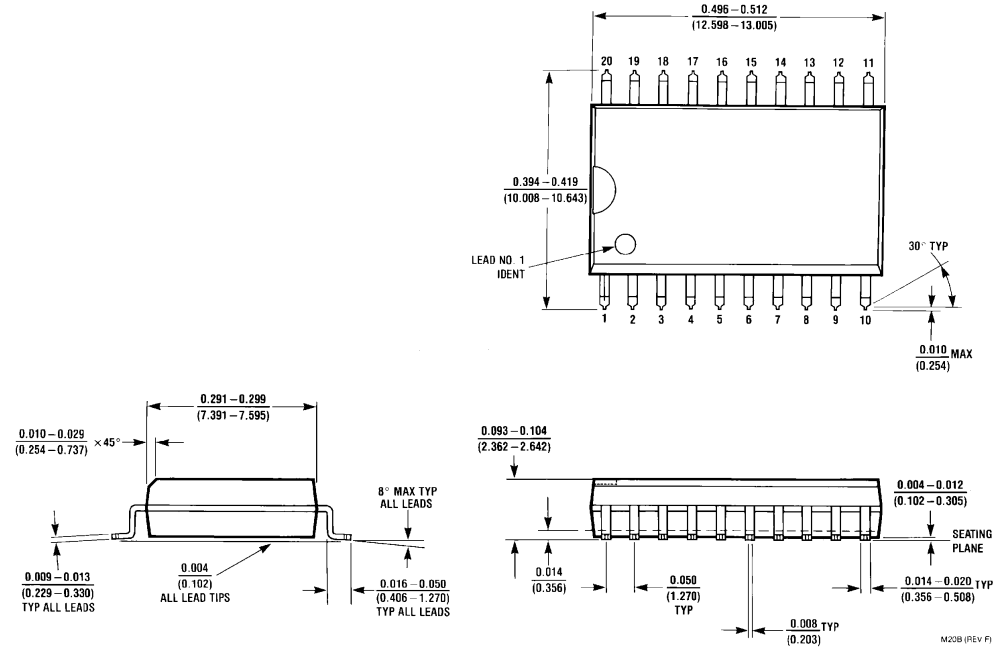
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		17	10			pF

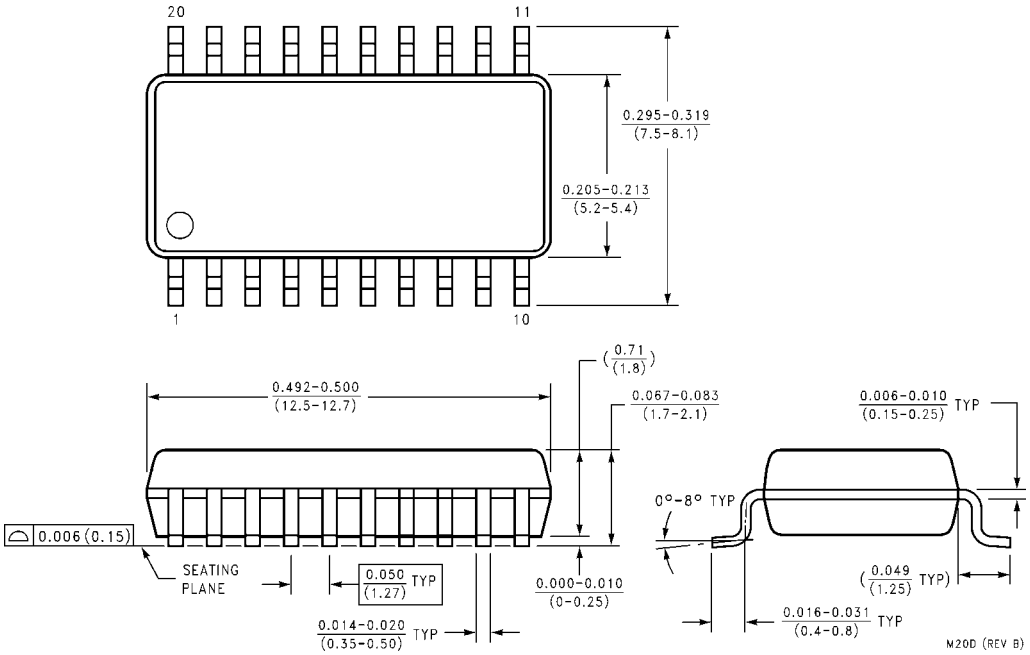
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per bit)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

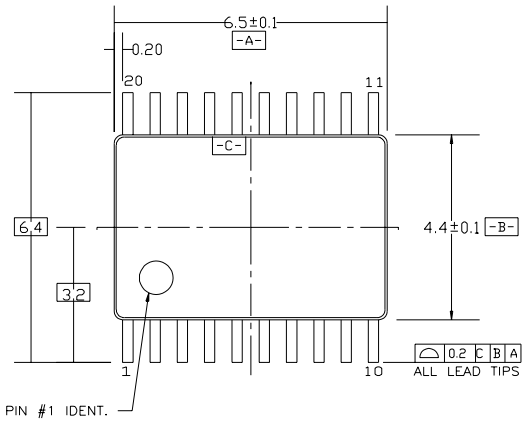


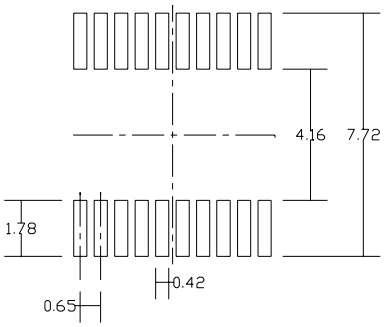
20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



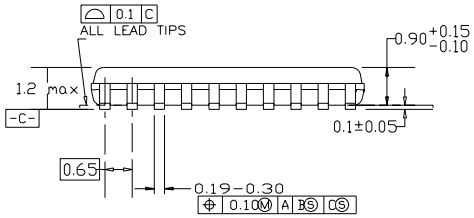
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

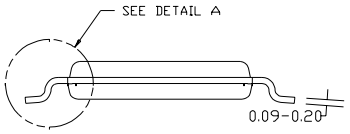
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

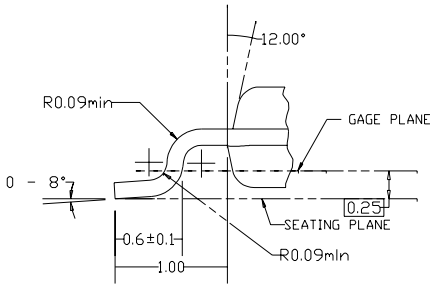




LAND PATTERN RECOMMENDATION







DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1993
Revised March 1999

74LVX244
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVX244 is an octal non-inverting buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

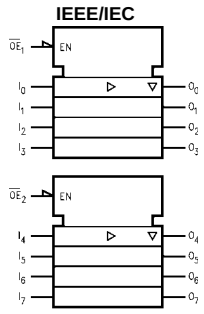
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

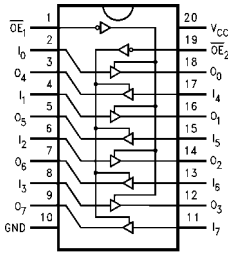
Order Number	Package Number	Package Description
74LVX244M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level L = LOW Voltage Level
X = Immaterial Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_o)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.5			1.5		V		
		3.0	2.0			2.0				
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5	V		
		3.0			0.8		0.8			
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output Off-State Current	3.6			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}	
									V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	2.7		6.1	11.4	1.0	13.5	ns	$C_L = 15$ pF
t_{PHL}	Time			8.6	14.9	1.0	17.0		$C_L = 50$ pF
		3.3 ± 0.3		4.7	7.1	1.0	8.5		$C_L = 15$ pF
				7.2	10.6	1.0	12.0		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		7.1	13.8	1.0	16.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			9.6	17.3	1.0	20.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		5.5	8.8	1.0	10.5		$C_L = 15$ pF, $R_L = 1$ kΩ
				8.0	12.3	1.0	14.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		11.6	16.0	1.0	19.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		9.7	11.4	1.0	13.0		
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

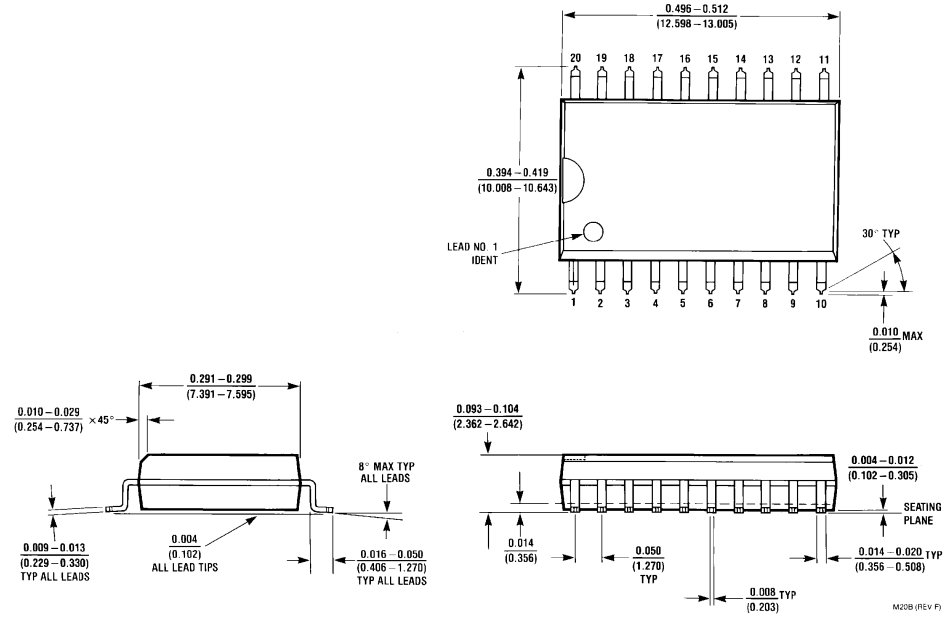
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		19				pF

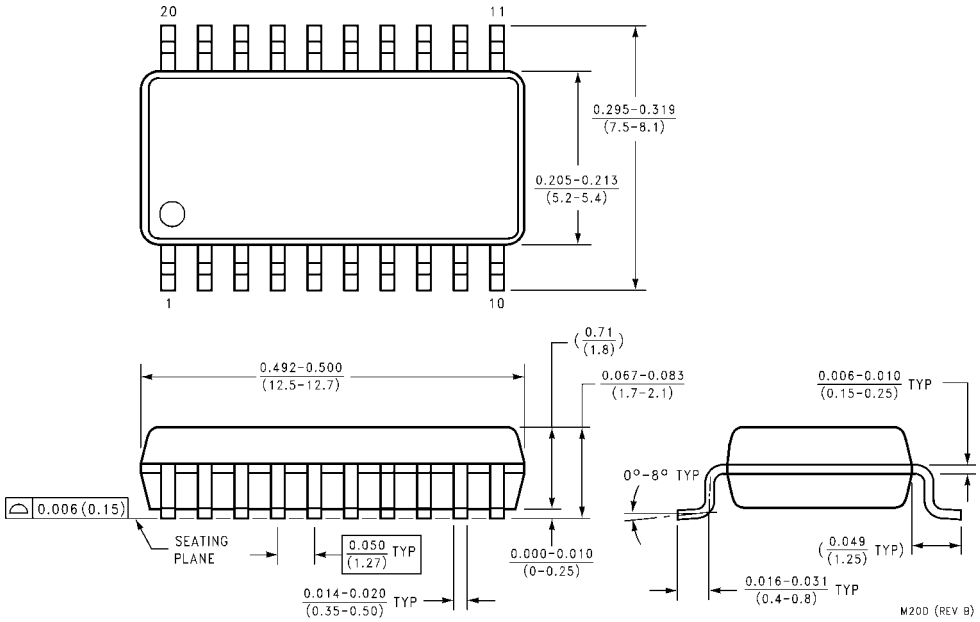
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per bit)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

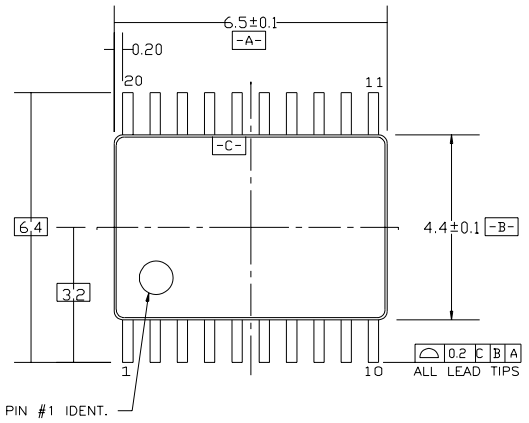


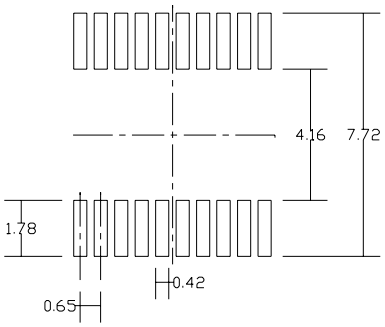
20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



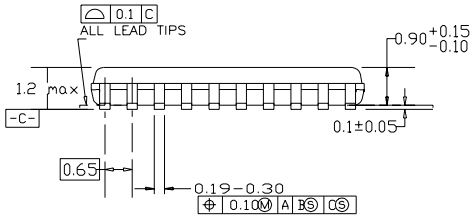
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

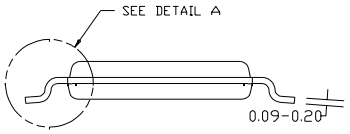
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

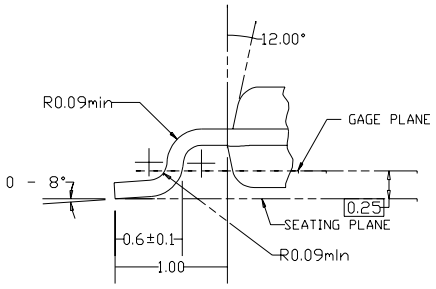




LAND PATTERN RECOMMENDATION







DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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April 1993
Revised March 1999

74LVX245
Low Voltage Octal Bidirectional Transceiver

General Description

The LVX245 contains eight non-inverting bidirectional buffers and is intended for bus-oriented applications. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a high impedance condition.

Features

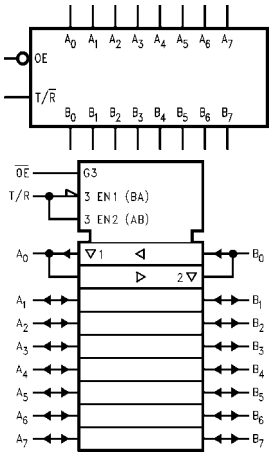
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code

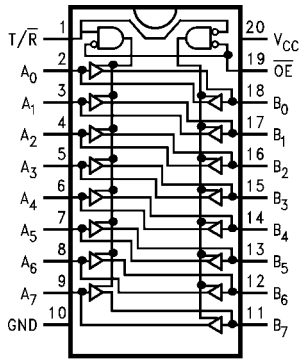
Order Number	Package Number	Package Description
74LVX245M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
$T/\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage T/$\overline{R}$, $\overline{OE}$ (V_I)	−0.5V to 7V
DC Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Bus I/O Voltage ($V_{I/O}$)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage T/$\overline{R}$, $\overline{OE}$ (V_I)	0V to 5.5V
Bus I/O Voltage ($V_{I/O}$)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input	3.0	2.0			2.0		V		
	Voltage	3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input	3.0			0.8		0.8	V		
	Voltage	3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
	Output	3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
	Voltage	3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
	Output	3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
	Voltage	3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE	3.6			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}	
	Output								V_{OUT} = V_{CC} or GND	
	Off-State Current									
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		6.1	10.7	1.0	13.5	ns	$C_L = 15$ pF
t_{PHL}				8.6	14.2	1.0	17.0		$C_L = 50$ pF
		3.3 ± 0.3		4.7	6.8	1.0	8.0		$C_L = 15$ pF
				7.2	10.1	1.0	11.5		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		9.0	16.9	1.0	20.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			11.5	20.4	1.0	24.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		7.1	11.0	1.0	13.0		$C_L = 15$ pF, $R_L = 1$ kΩ
				9.6	14.5	1.0	16.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		11.5	18.0	1.0	21.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		9.6	12.8	1.0	14.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	$C_L = 50$ pF (Note 4)
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

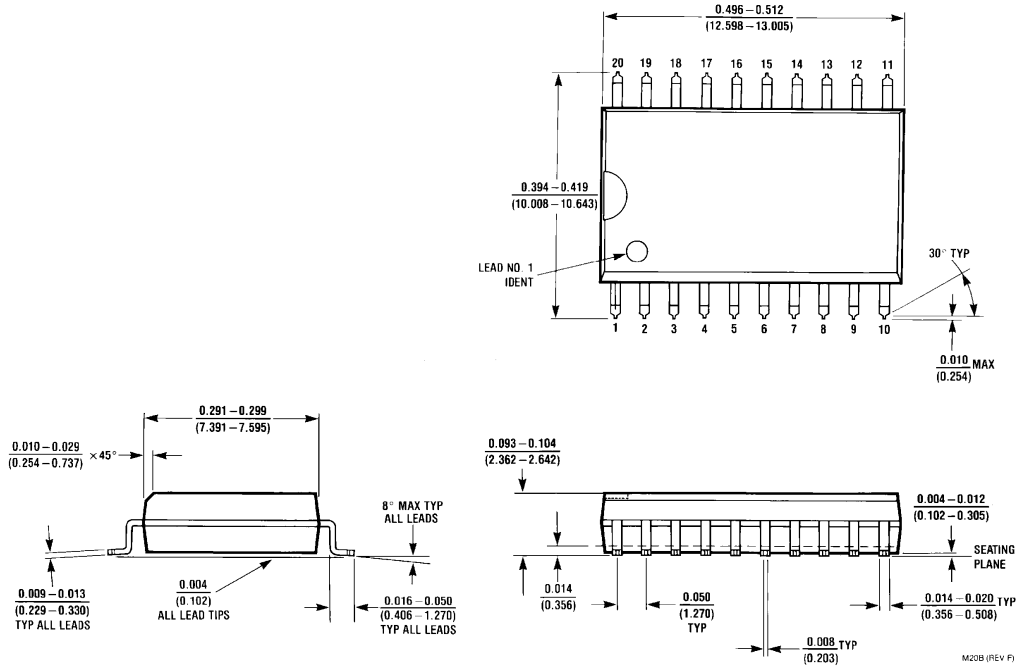
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance $T/\overline{R}$, $\overline{OE}$		4	10		10	pF
$C_{I/O}$	Output Capacitance A_n, B_n		8				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		21				pF

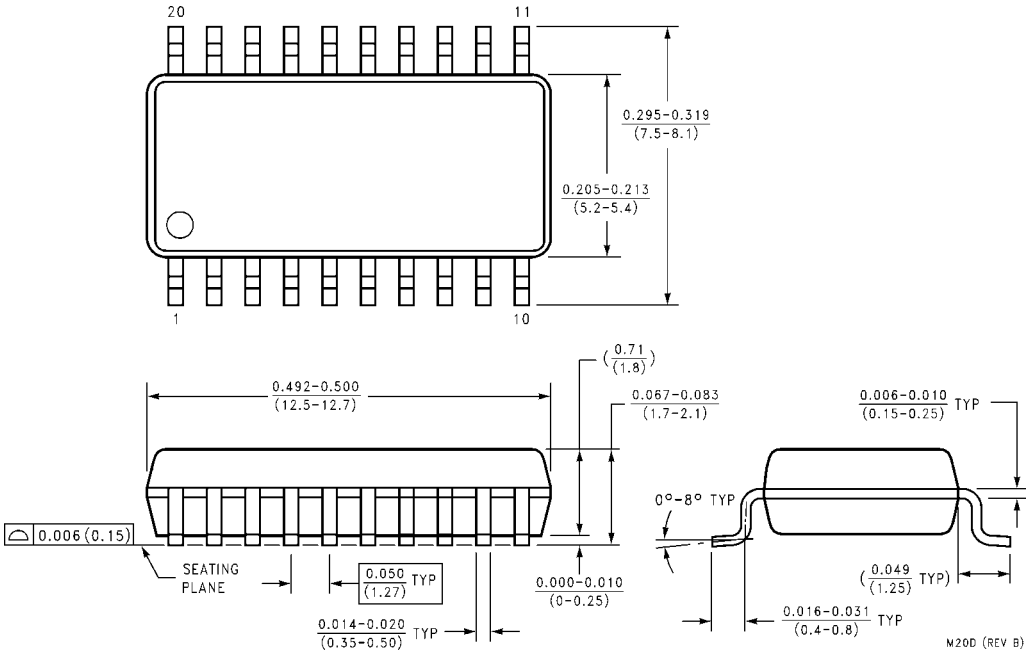
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \dfrac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per bit)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

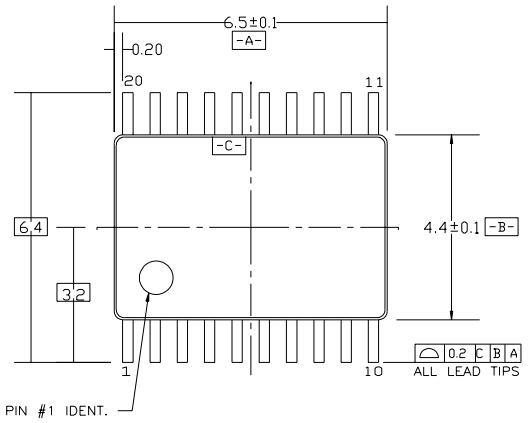


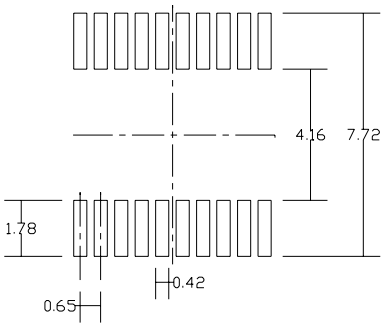
20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



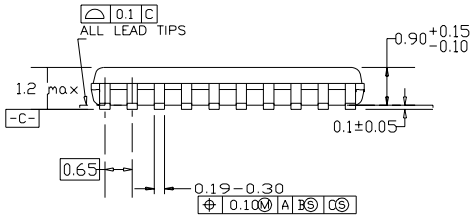
20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

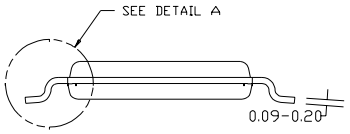
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

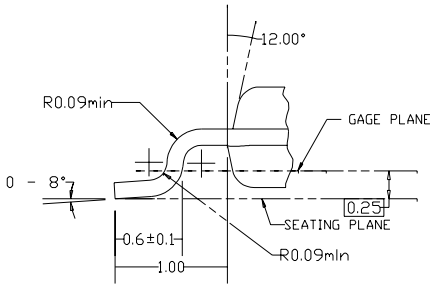




LAND PATTERN RECOMMENDATION







DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1993
Revised March 1999

74LVX273
Low Voltage Octal D-Type Flip-Flop

General Description

The LVX273 has eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) and Master Reset ($\overline{MR}$) input load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output.

All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input. The device is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

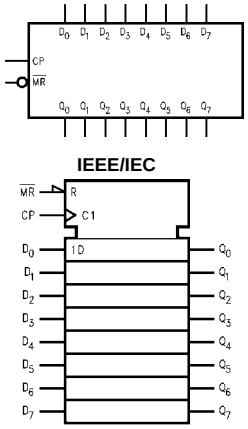
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

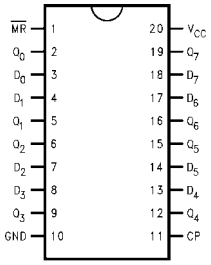
Order Number	Package Number	Package Description
74LVX273M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending letter suffix "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

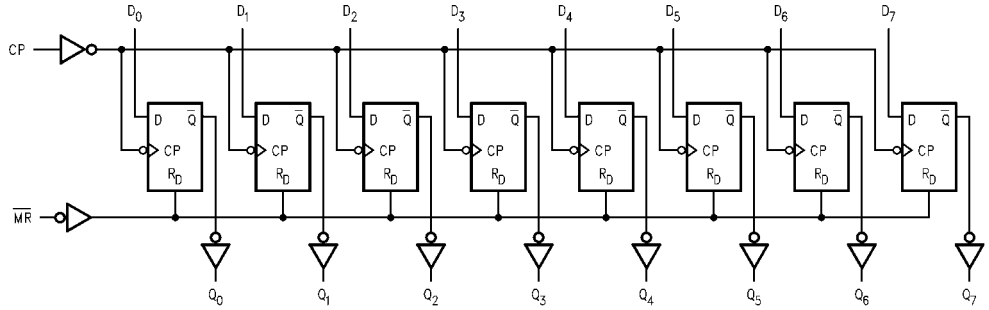
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

Truth Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load '1'	H	⌐	H	H
Load '0'	H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output	3.6			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		9.0	16.9	1.0	20.5	ns	15
t_{PHL}	Delay Time			11.5	20.0	1.0	24.0		50
	CP to Q_n	3.3 ± 0.3		7.1	11.0	1.0	13.0		15
				9.6	14.5	1.0	16.5		50
t_{PHL}	Propagation Delay	2.7		9.3	17.8	1.0	20.5	ns	15
	$\overline{MR}$ to Q_n			11.8	21.1	1.0	24.0		50
		3.3 ± 0.3		7.3	11.5	1.0	13.5		15
				9.8	15.0	1.0	17.0		50
t_S	Setup Time	2.7	8.0			9.5		ns	
	D_n to CP	3.3 ± 0.3	5.5			6.5			
t_H	Hold Time	2.7	1.0			1.0		ns	
	D_n to CP	3.3 ± 0.3	1.0			1.0			
t_{REC}	Removal Time	2.7	4.0			4.0		ns	
	$\overline{MR}$ to CP	3.3 ± 0.3	2.5			2.5			
t_W	Clock Pulse	2.7	8.0			9.5		ns	
	Width	3.3 ± 0.3	5.5			6.5			
t_W	$\overline{MR}$ Pulse	2.7	7.5			8.5		ns	
	Width	3.3 ± 0.3	5.0			6.0			
f_{MAX}	Maximum	2.7	55	110		45		MHz	15
	Clock		45	60		40			50
	Frequency	3.3 ± 0.3	95	150		80			15
			60	90		50			50
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

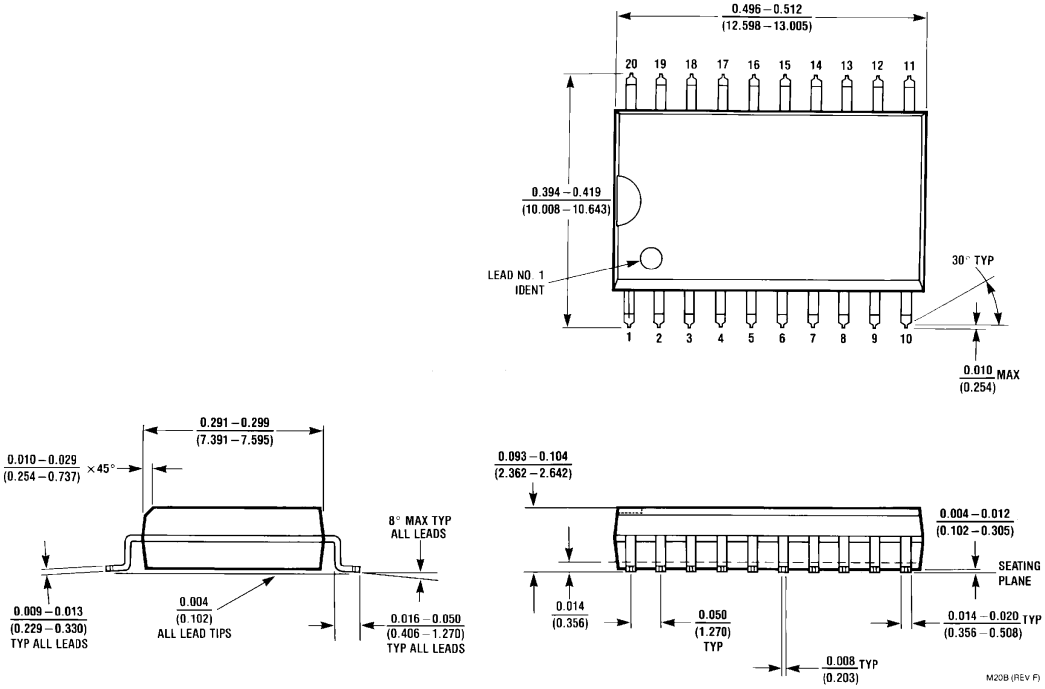
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		31				pF

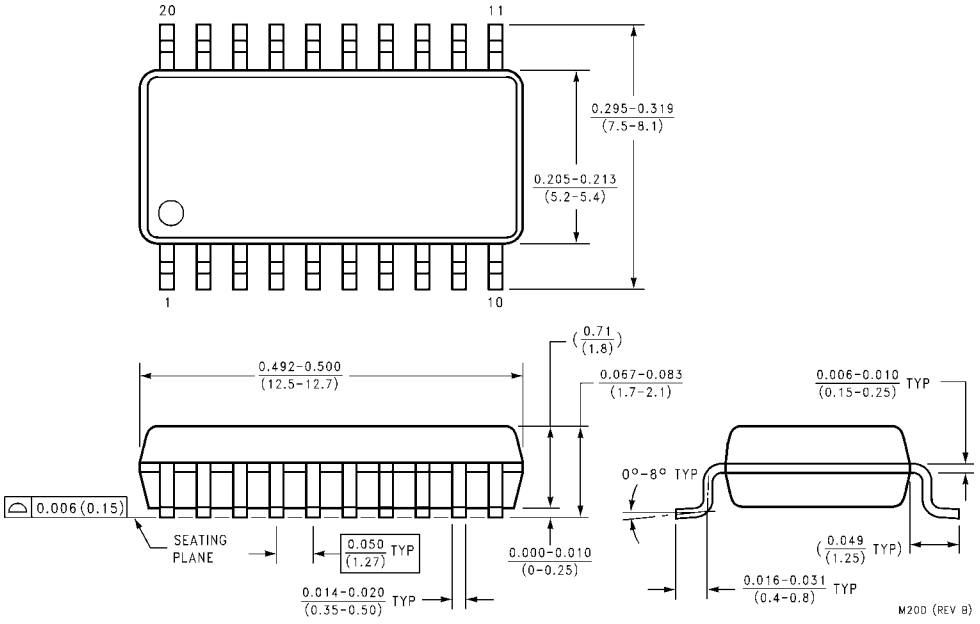
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per F/F)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

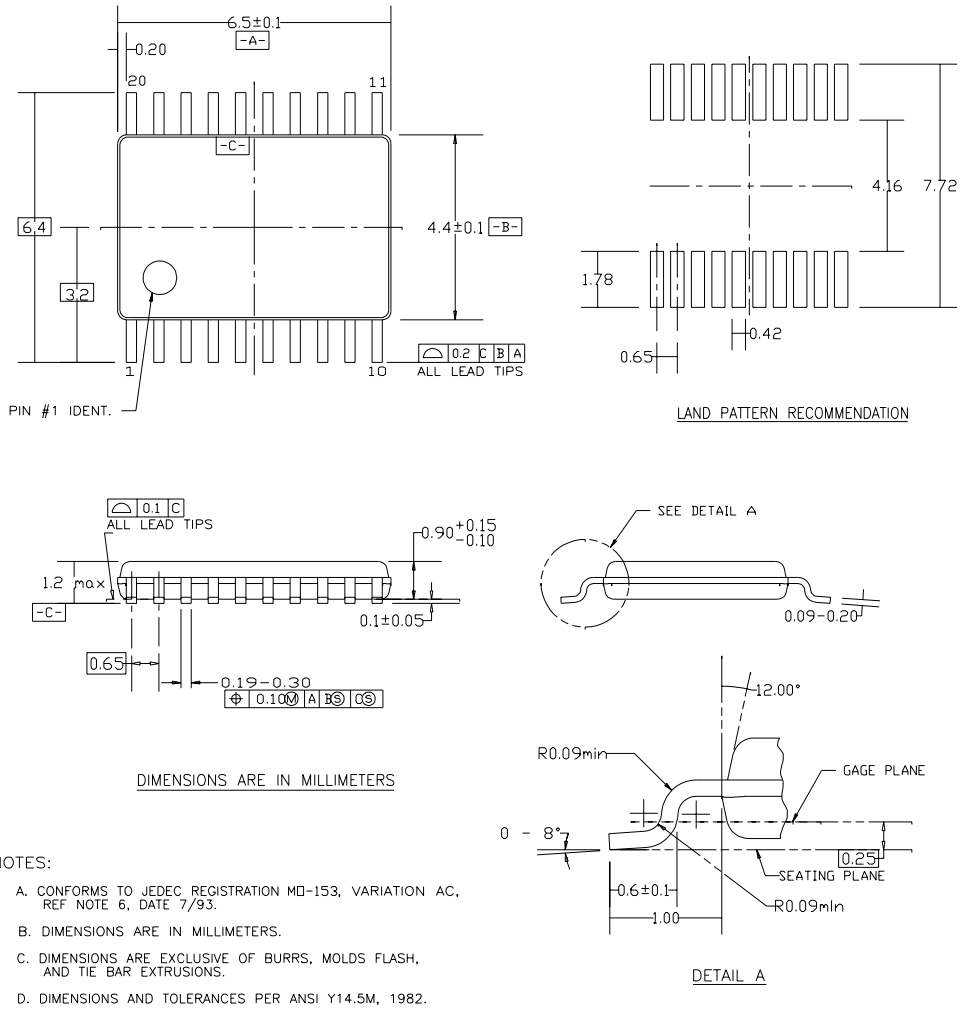


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX32
Low Voltage Quad 2-Input OR Gate

General Description

The LVX32 contains four 2-input OR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

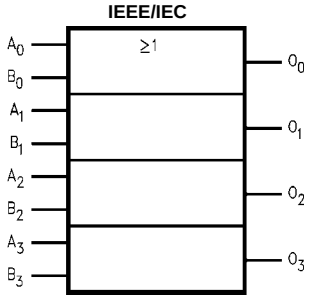
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

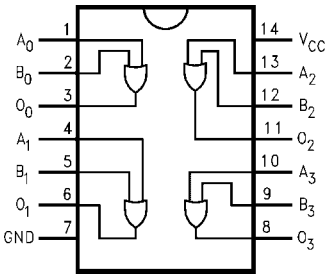
Order Number	Package Number	Package Description
74LVX32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.5			1.5		V		
		3.0	2.0			2.0				
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5	V		
		3.0			0.8		0.8			
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: (Input t_r = t_f = 3 ns)

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		5.8	10.7	1.0	12.5	ns	15
t_{PHL}	Delay Time			8.3	14.2	1.0	16.0		50
		3.3 ± 0.3		4.4	6.6	1.0	7.5		15
				6.9	10.1	1.0	11.5		50
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

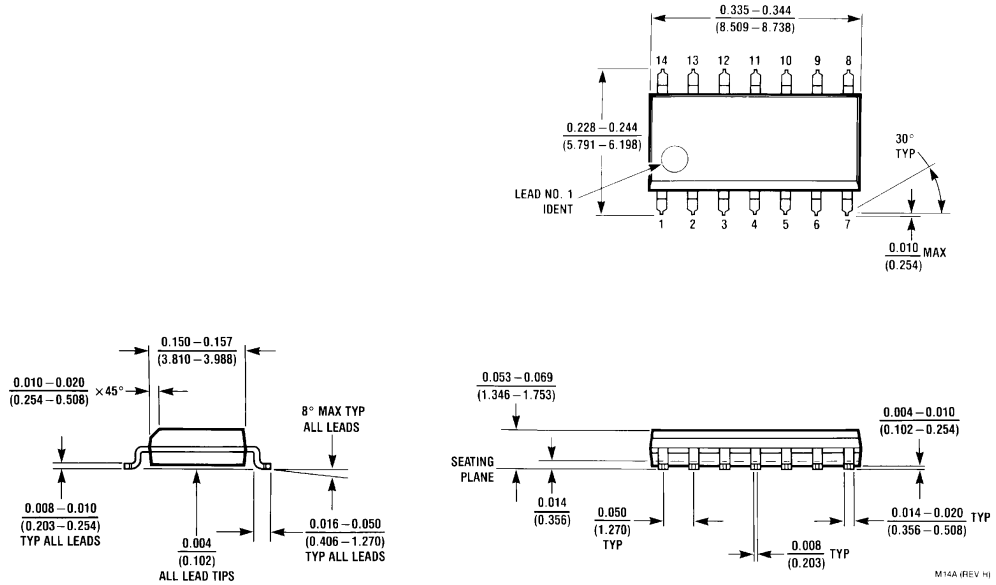
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		14				pF

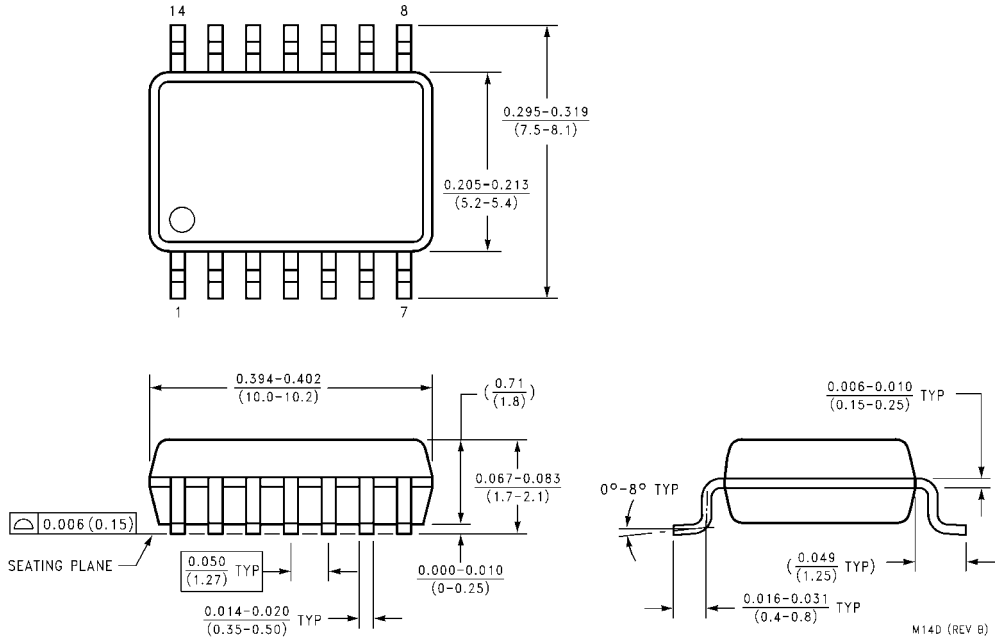
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per Gate)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

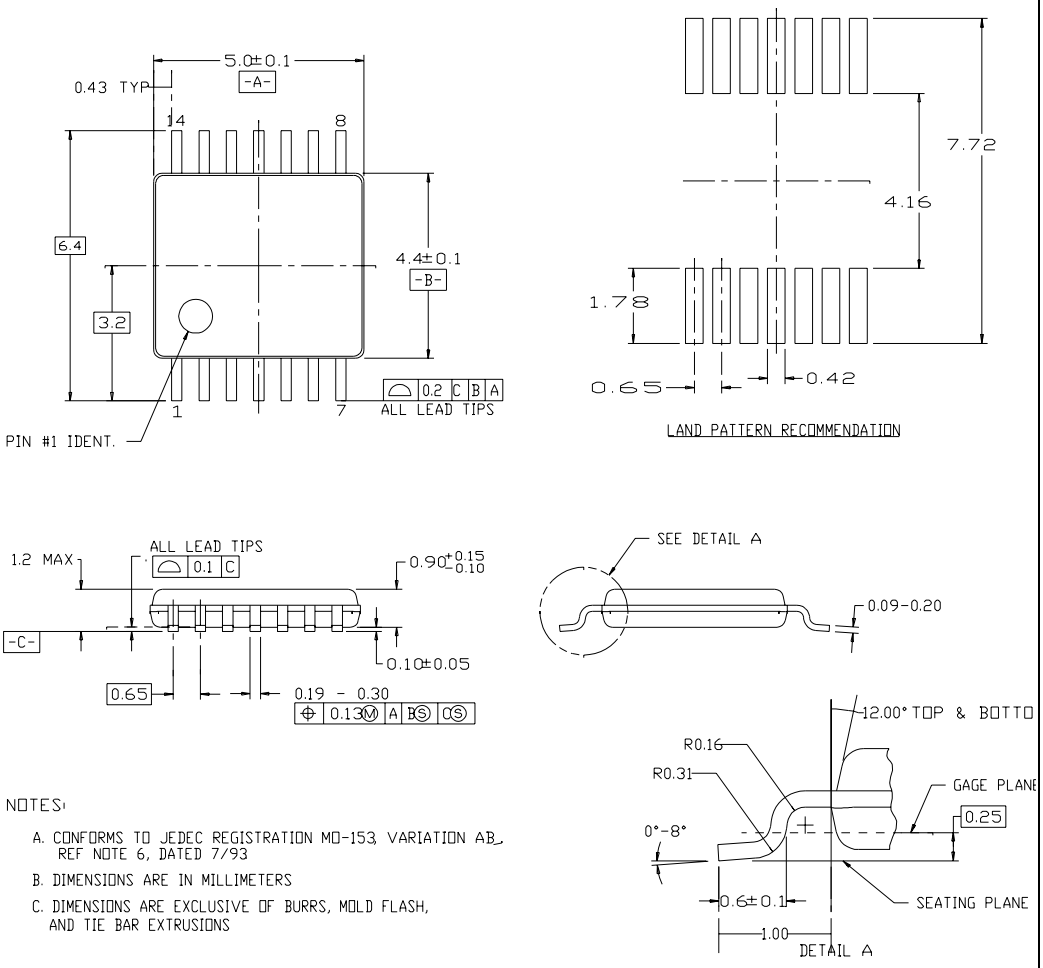


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

July 1993
Revised July 1999

74LVX3245
8-Bit Dual Supply Translating Transceiver with 3-STATE Outputs

General Description

The LVX3245 is a dual-supply, 8-bit translating transceiver that is designed to interface between a 3V bus and a 5V bus in a mixed 3V/5V supply environment. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a high impedance condition. The A Port interfaces with the 3V bus; the B Port interfaces with the 5V bus.

The LVX3245 is suitable for mixed voltage applications such as notebook computers using 3.3V CPU and 5V peripheral components.

Features

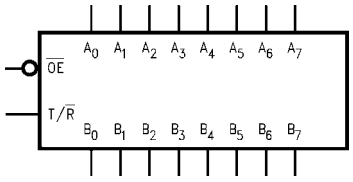
- Bidirectional interface between 3V and 5V buses
- Inputs compatible with TTL level
- 3V data flow at A Port and 5V data flow at B Port
- Outputs source/sink 24 mA
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Implements proprietary EMI reduction circuitry
- Functionally compatible with the 74 series 245

Ordering Code:

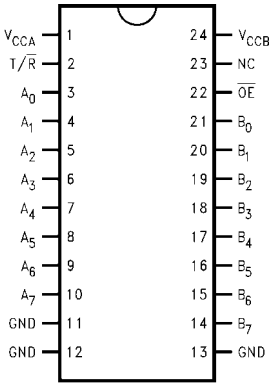
Order Number	Package Number	Package Description
74LVX3245WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX3245QSC	MQA24	24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74LVX3245MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

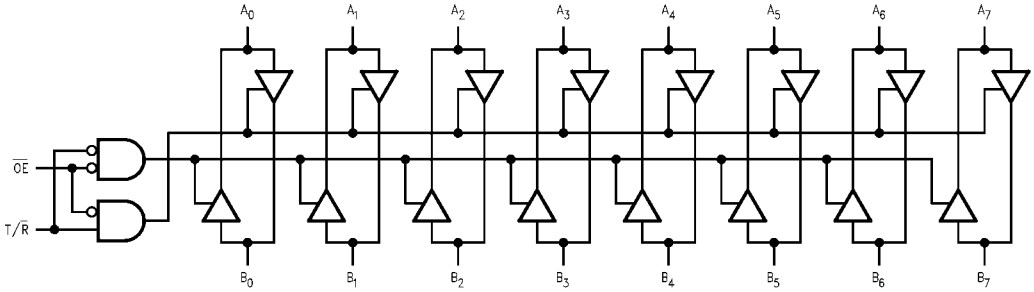
Pin Names	Description
$\overline{OE}$	Output Enable Input
$T/\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CCA}, V_{CCB})	−0.5V to +7.0V
DC Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	−0.5V to V_{CCA} + 0.5V
DC Input/Output Voltage ($V_{I/O}$)	
@ A_n	−0.5V to V_{CCA} + 0.5V
@ B_n	−0.5V to V_{CCB} + 0.5V
DC Input Diode Current (I_{IN})	
@ $\overline{OE}$, T/$\overline{R}$	±20 mA
DC Output Diode Current (I_{OK})	±50 mA
DC Output Source or	
Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
and Max Current @ I_{CCA}	±100 mA
@ I_{CCB}	±200 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage	
V_{CCA}	2.7V to 3.6V
V_{CCB}	4.5V to 5.5V
Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	0V to V_{CCA}
Input/Output Voltage ($V_{I/O}$)	
@ A_n	0V to V_{CCA}
@ B_n	0V to V_{CCB}
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	8 ns/V
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused Pins (inputs and I/Os) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	T_A = +25°C Typ	T_A = −40°C to +85°C Guaranteed Limits		Units	Conditions
V_{IHA}	Minimum HIGH Level Input Voltage	A_n, T/$\overline{R}$, $\overline{OE}$	3.6	5.0		2.0	2.0	V	V_{OUT} ≤ 0.1V or ≥ V_{CC} − 0.1V
			2.7	5.0		2.0	2.0		
V_{IHB}		B_n	3.3	4.5		2.0	2.0		
			3.3	5.5		2.0	2.0		
V_{ILA}	Maximum LOW Level Input Voltage	A_n, T/$\overline{R}$, $\overline{OE}$	3.6	5.0		0.8	0.8	V	V_{OUT} ≤ 0.1V or ≥ V_{CC} −0.1V
			2.7	5.0		0.8	0.8		
V_{ILB}		B_n	3.3	4.5		0.8	0.8		
			3.3	5.5		0.8	0.8		
V_{OHA}	Minimum HIGH Level Output Voltage		3.0	4.5	2.99	2.9	2.9	V	I_{OUT} = −100 µA
			3.0	4.5	2.65	2.35	2.25		I_{OH} = −24 mA
			2.7	4.5	2.5	2.3	2.2		I_{OH} = −12 mA
			2.7	4.5	2.3	2.1	2.0		I_{OH} = −24 mA
V_{OHB}			3.0	4.5	4.5	4.4	4.4	V	I_{OUT} = −100 µA
			3.0	4.5	4.25	3.86	3.76		I_{OH} = −24 mA
V_{OLA}	Maximum LOW Level Output Voltage		3.0	4.5	0.002	0.1	0.1	V	I_{OUT} =100 µA
			3.0	4.5	0.21	0.36	0.44		I_{OL} = 24 mA
			2.7	4.5	0.11	0.36	0.44		I_{OL} = 12 mA
			2.7	4.5	0.22	0.42	0.5		I_{OL} = 24 mA
V_{OLB}			3.0	4.5	0.002	0.1	0.1	V	I_{OUT} = 100 µA
			3.0	4.5	0.18	0.36	0.44		I_{OL} = 24 mA
I_{IN}	Maximum Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		3.6	5.5		±0.1	±1.0	µA	V_I = V_{CCB}, GND
I_{OZA}	Maximum 3-STATE Output Leakage @ A_n		3.6	5.5		±0.5	±5.0	µA	V_I = V_{IL}, V_{IH} $\overline{OE}$ = V_{CCA} V_O = V_{CCA}, GND
I_{OZB}	Maximum 3-STATE Output Leakage @ B_n		3.6	5.5		±0.5	±5.0	µA	V_I = V_{IL}, V_{IH} $\overline{OE}$ = V_{CCA} V_O = V_{CCB}, GND

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	$T_A = +25°C$ Typ	$T_A = +25°C$ Guaranteed Limits	$T_A = -40°C$ to $+85°C$ Guaranteed Limits	Units	Conditions
ΔI_{CC}	Maximum	B_n	3.6	5.5	1.0	1.35	1.5	mA	$V_I = V_{CCB} - 2.1V$
	I_{CCT}/Input @	A_n, $T/\overline{R}$, $\overline{OE}$	3.6	5.5		0.35	0.5	mA	$V_I = V_{CCA} - 0.6V$
I_{CCA}	Quiescent V_{CCA} Supply Current		3.6	5.5		5	50	µA	$A_n = V_{CCA}$ or GND, $B_n = V_{CCB}$ or GND, $\overline{OE}$ = GND, $T/\overline{R}$ = GND
I_{CCB}	Quiescent V_{CCB} Supply Current		3.6	5.5		8	80	µA	$A_n = V_{CCA}$ or GND, $B_n = V_{CCB}$ or GND, $\overline{OE}$ = GND, $T/\overline{R} = V_{CCA}$
V_{OLPA}	Quiet Output Maximum		3.3	5.0		0.8		V	(Note 3) (Note 4)
V_{OLPB}	Dynamic V_{OL}		3.3	5.0		1.5			
V_{OLVA}	Quiet Output Minimum		3.3	5.0		–0.8		V	(Note 3) (Note 4)
V_{OLVB}	Dynamic V_{OL}		3.3	5.0		–1.2			
V_{IHDA}	Minimum HIGH Level		3.3	5.0		2.0		V	(Note 3) (Note 5)
V_{IHDB}	Dynamic Input Voltage		3.3	5.0		2.0			
V_{ILDA}	Maximum LOW Level		3.3	5.0		0.8		V	(Note 3) (Note 5)
V_{ILDB}	Dynamic Input Voltage		3.3	5.0		0.8			

Note 3: Worst case package.

Note 4: Max number of outputs defined as (n). Data inputs are driven 0V to V_{CC} level; one output at GND.

Note 5: Max number of Data Inputs (n) switching. (n–1) inputs switching 0V to V_{CC} level. Input-under-test switching: V_{CC} level to threshold (V_{IHD}), 0V to threshold (V_{ILD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameters	$T_A = +25°C$, $C_L = 50$ pF, $V_{CCA} = 3.3V$ (Note 6), $V_{CCB} = 5.0V$ (Note 7)			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $V_{CCA} = 3.3V$ (Note 6), $V_{CCB} = 5.0V$ (Note 7)		$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $V_{CCA} = 2.7V$, $V_{CCB} = 5.0V$ (Note 7)		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.0	5.4	8.0	1.0	8.5	1.0	9.0	ns
t_{PLH}	A to B	1.0	5.6	7.5	1.0	8.0	1.0	8.5	
t_{PHL}	Propagation Delay	1.0	5.1	7.5	1.0	8.0	1.0	8.5	ns
t_{PLH}	B to A	1.0	5.7	7.5	1.0	8.0	1.0	8.5	
t_{PZL}	Output Enable	1.0	4.8	8.0	1.0	8.5	1.0	9.0	ns
t_{PZH}	Time $\overline{OE}$ to B	1.0	6.3	8.5	1.0	9.0	1.0	9.5	
t_{PZL}	Output Enable	1.0	6.3	8.5	1.0	9.0	1.0	9.5	ns
t_{PZH}	Time $\overline{OE}$ to A	1.0	6.8	9.0	1.0	9.5	1.0	10.0	
t_{PHZ}	Output Disable	1.0	5.3	7.5	1.0	8.0	1.0	8.5	ns
t_{PLZ}	Time $\overline{OE}$ to B	1.0	4.2	7.0	1.0	7.5	1.0	8.0	
t_{PHZ}	Output Disable	1.0	5.3	8.0	1.0	8.5	1.0	9.0	ns
t_{PLZ}	Time $\overline{OE}$ to A	1.0	3.7	6.5	1.0	7.0	1.0	7.5	
t_{OSHL}	Output to Output								
t_{OSLH}	Skew (Note 8)		1.0	1.5		1.5		1.5	ns
	Data to Output								

Note 6: Voltage Range 3.3V is 3.3V ± 0.3V.

Note 7: Voltage Range 5.0V is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

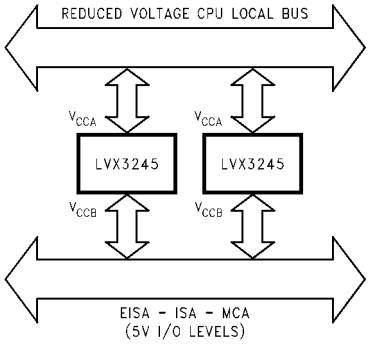
Symbol	Parameter		Typ	Units	Conditions
C_{IN}	Input Capacitance		4.5	pF	V_{CC} = Open
$C_{I/O}$	Input/Output Capacitance		15	pF	V_{CCA} = 3.3V V_{CCB} = 5.0V
C_{PD}	Power Dissipation Capacitance (Note 9)	A → B	55	pF	V_{CCB} = 5.0V
		B → A	40		V_{CCA} = 3.3V

Note 9: C_{PD} is measured at 10 MHz

8-Bit Dual Supply Translating Transceiver

The LVX3245 is a dual supply device capable of bidirectional signal translation. This level shifting ability provides an efficient interface between low voltage CPU local bus with memory and a standard bus defined by 5V I/O levels. The device control inputs can be controlled by either the low voltage CPU and core logic or a bus arbitrator with 5V I/O levels.

Manufactured on a sub-micron CMOS process, the LVX3245 is ideal for mixed voltage applications such as notebook computers using 3.3V CPU's and 5V peripheral devices.



Power Up Considerations

To insure that the system does not experience unnecessary I_{CC} current draw, bus contention, or oscillations during power up, the following guidelines should be adhered to (refer to Table 1):

- Power up the control side of the device first. This is the V_{CCA}.
- $\overline{OE}$ should ramp with or ahead of V_{CCA}. This will help guard against bus contention.
- The Transmit/Receive control pin (T/$\overline{R}$) should ramp with V_{CCA}, this will ensure that the A Port data pins are configured as inputs. With V_{CCA} receiving power first, the A I/O Port should be configured as inputs to help guard against bus contention and oscillations.
- A side data inputs should be driven to a valid logic level. This will prevent excessive current draw.

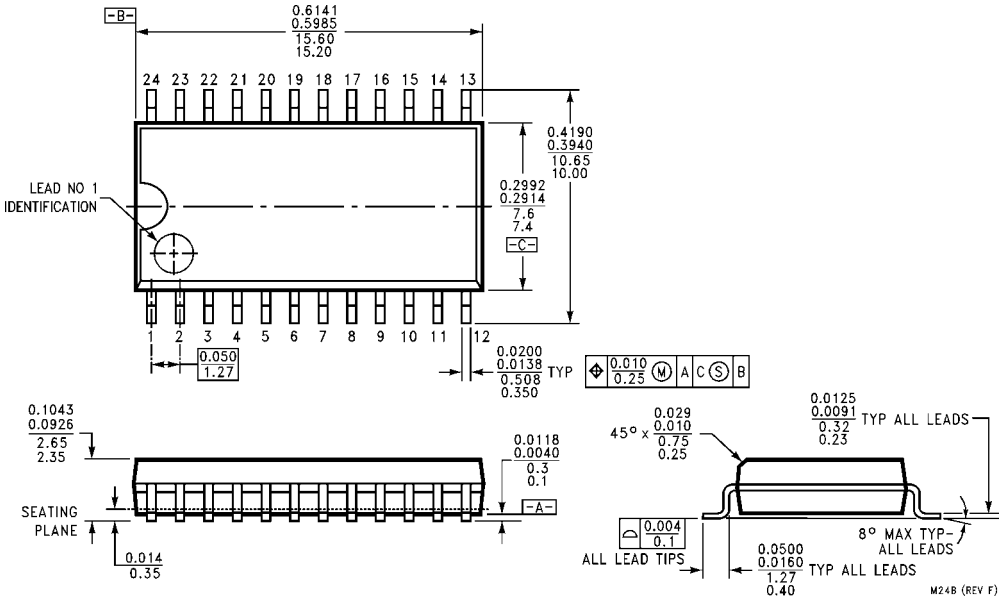
The above steps will ensure that no bus contention or oscillations, and therefore no excessive current draw occurs during the power up cycling of these devices. These steps will help prevent possible damage to the translator devices and potential damage to other system components.

TABLE 1. Low Voltage Translator Power Up Sequencing Table

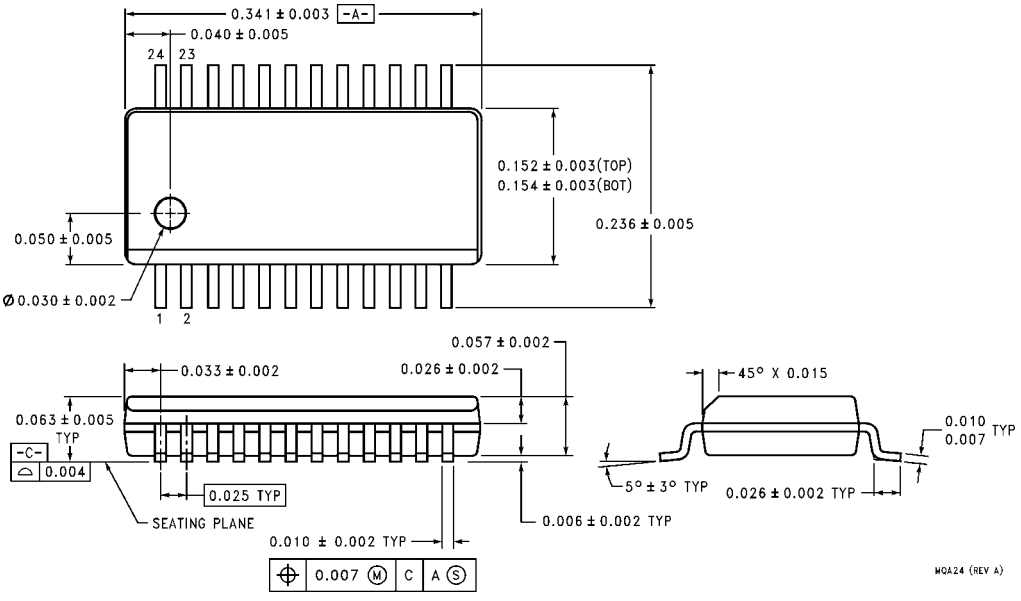
Device Type	V_{CCA}	V_{CCB}	T/$\overline{R}$	$\overline{OE}$	A Side I/O	B Side I/O	Floatable Pin Allowed
74LVX3245	3V (power up 1st)	5V configurable	ramp with V_{CCA}	ramp with V_{CCA}	logic 0V or V_{CCA}	outputs	No

Please reference Application Note AN-5001 for more detailed information on using Fairchild's LVX Low Voltage Dual Supply CMOS Translating Transceivers.

Physical Dimensions inches (millimeters) unless otherwise noted

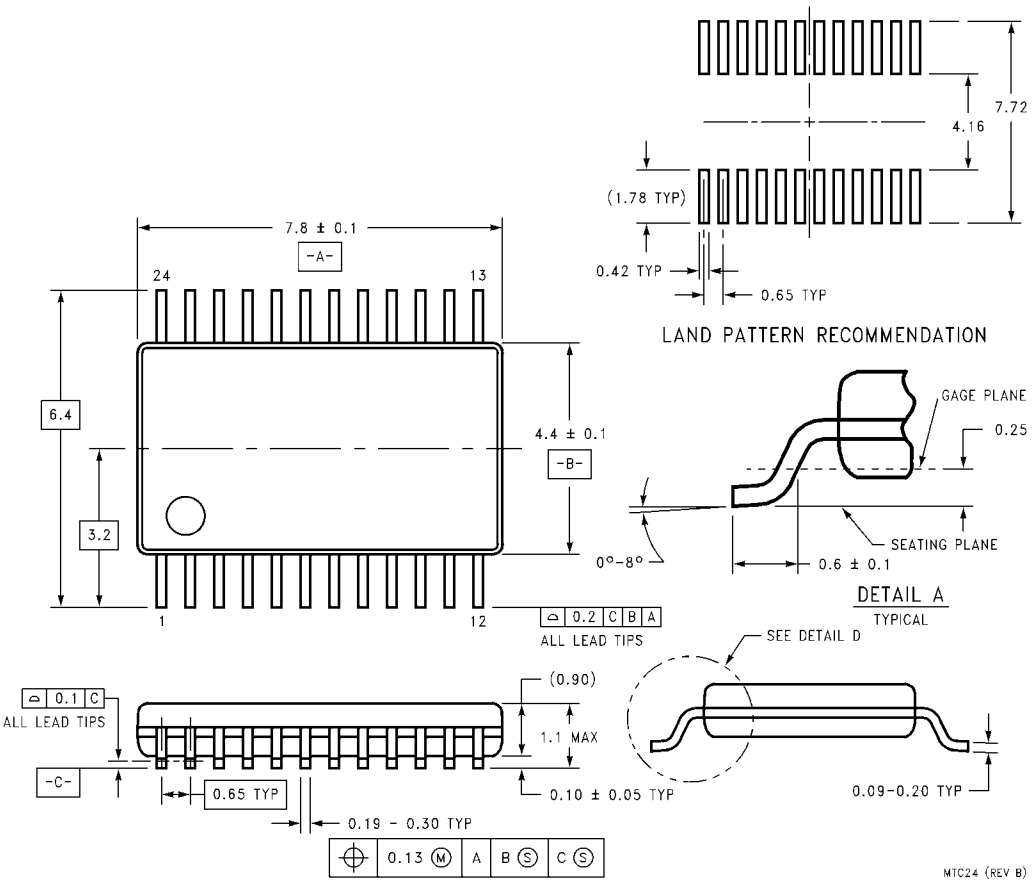


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

LIFE SUPPORT POLICY

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FAIRCHILD SEMICONDUCTOR™

June 1993
Revised March 1999

74LVX373
Low Voltage Octal Transparent Latch with 3-STATE Outputs

General Description

The LVX373 consists of eight latches with 3-STATE outputs for bus organized system applications. The latches appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the bus output is in the high impedance state. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

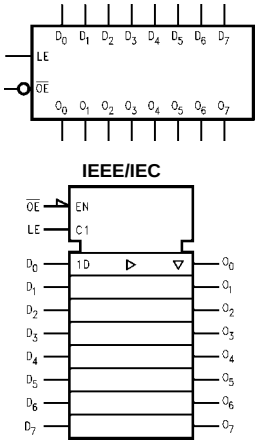
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications

Ordering Code:

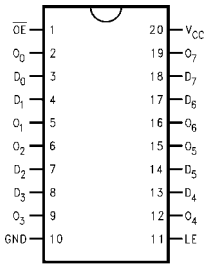
Order Number	Package Number	Package Description
74LVX373M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Functional Description

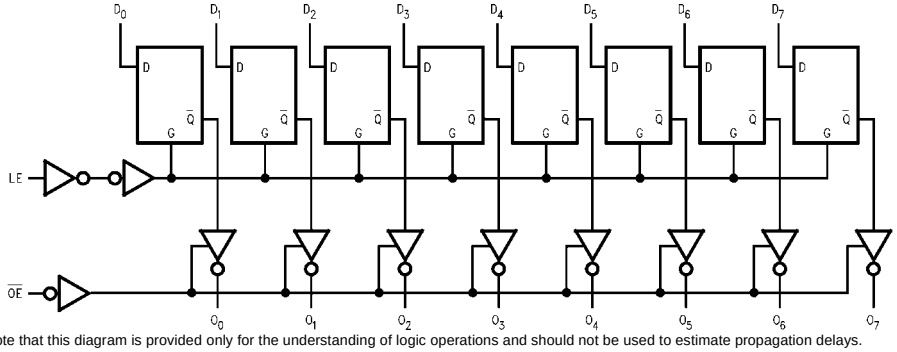
The LVX373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output	3.6			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	2.7		7.7	15.0	1.0	18.5	ns	$C_L = 15$ pF
t_{PHL}	D_n to O_n			10.2	18.5	1.0	22.0		$C_L = 50$ pF
		3.3 ± 0.3		6.0	9.7	1.0	11.5		$C_L = 15$ pF
				8.5	13.2	1.0	15.0		$C_L = 50$ pF
t_{PLH}	Propagation Delay Time	2.7		7.5	14.5	1.0	17.5	ns	$C_L = 15$ pF
t_{PHL}	LE to O_n			10.0	18.0	1.0	21.0		$C_L = 50$ pF
		3.3 ± 0.3		5.8	9.3	1.0	11.0		$C_L = 15$ pF
				8.3	12.8	1.0	14.5		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		7.7	15.0	1.0	18.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			10.2	18.5	1.0	22.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		6.0	9.7	1.0	11.5		$C_L = 15$ pF, $R_L = 1$ kΩ
				8.5	13.2	1.0	15.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		9.8	18.0	1.0	21.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		8.2	12.8	1.0	14.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_W	LE Pulse Width, HIGH	2.7	6.5			7.5		ns	
		3.3 ± 0.3	5.0			5.0			
t_S	Setup Time, D_n to LE	2.7	6.0			6.0		ns	
		3.3 ± 0.3	4.0			4.0			
t_H	Hold Time, D_n to LE	2.7	1.0			1.0		ns	
		3.3 ± 0.3	1.0			1.0			
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

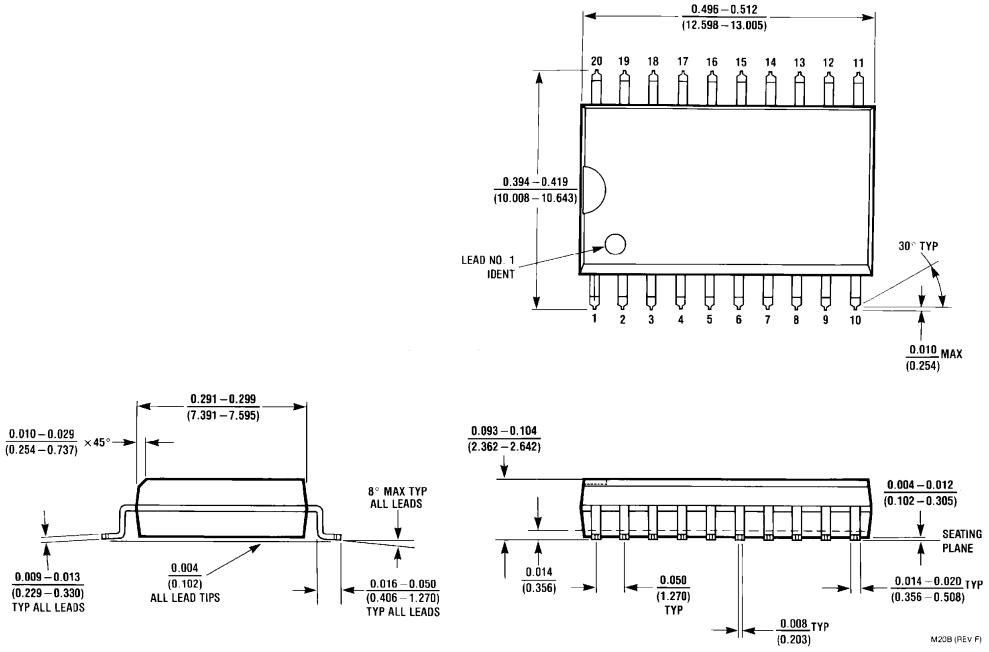
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		27				pF

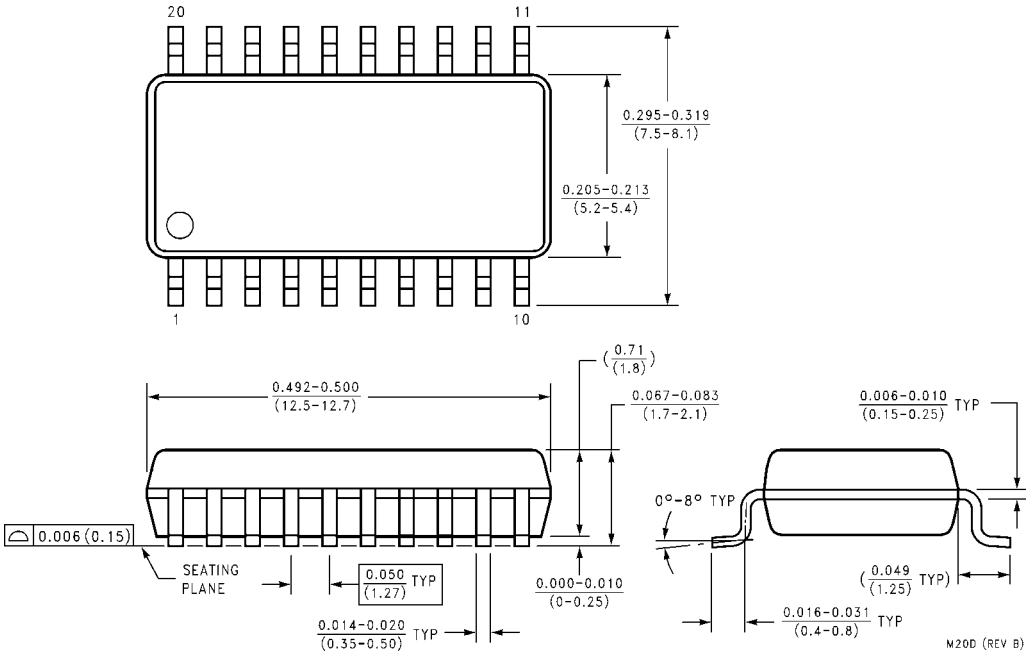
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \dfrac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per Latch)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

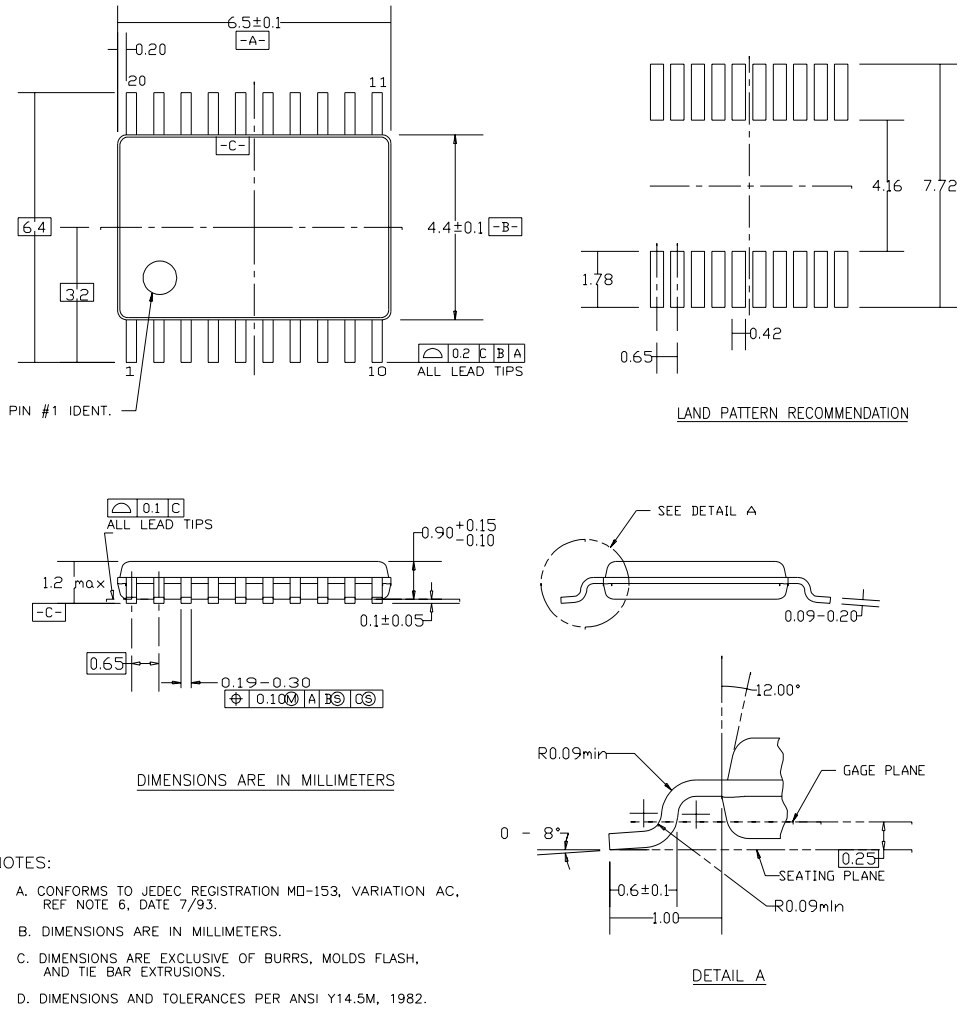


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1993
Revised March 1999

74LVX374
Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVX374 is a high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

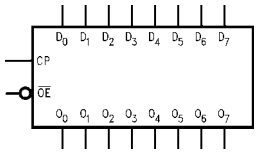
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

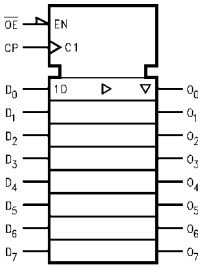
Order Number	Package Number	Package Description
74LVX374M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

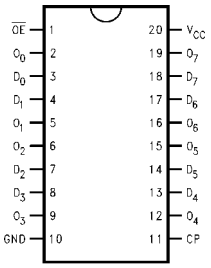
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

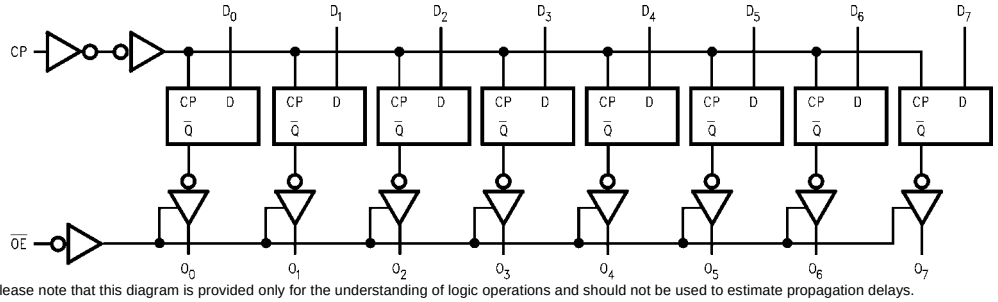
Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Functional Description

The LVX374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH}	I_{OH} = − 50μA
	Output Voltage	3.0	2.9	3.0		2.9		V	or V_{IL}	I_{OH} = −50μA
		3.0	2.58			2.48				I_{OH} = −4mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH}	I_{OL} = 50μA
	Output Voltage	3.0		0.0	0.1		0.1	V	or V_{IL}	I_{OL} = 50μA
		3.0			0.36		0.44			I_{OL} = 4mA
I_{OZ}	3-STATE Output	3.6			±0.25		±2.5		V_{IN} = V_{IH} or V_{IL}	
	Off-State Current							μA	V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock Frequency	2.7	60	115		50		MHz	$C_L = 15$ pF
			45	60		40			$C_L = 50$ pF
		3.3 ± 0.3	100	160		85			$C_L = 15$ pF
			60	95		55			$C_L = 50$ pF
t_{PLH} t_{PHL}	Propagation Delay Time CP to O_n	2.7		8.5	16.3	1.0	19.5	ns	$C_L = 15$ pF
				11.0	19.8	1.0	23.0		$C_L = 50$ pF
		3.3 ± 0.3		6.7	10.6	1.0	12.5		$C_L = 15$ pF
				9.2	14.1	1.0	16.0		$C_L = 50$ pF
t_{PZL} t_{PZH}	3-STATE Output Enable Time	2.7		7.6	14.5	1.0	17.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
				10.1	18.0	1.0	21.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		5.9	9.3	1.0	11.0		$C_L = 15$ pF, $R_L = 1$ kΩ
				8.4	12.8	1.0	14.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ} t_{PHZ}	3-STATE Output Disable Time	2.7		11.5	18.5	1.0	22.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		9.6	13.2	1.0	15.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_W	CP Pulse Width	2.7	7.5			8.0		ns	
		3.3 ± 0.3	5.0			5.5			
t_S	Setup Time D_n to CP	2.7	6.5			6.5		ns	
		3.3 ± 0.3	4.5			4.5			
t_H	Hold Time D_n to CP	2.7	2.0			2.0		ns	
		3.3 ± 0.3	2.0			2.0			
t_{OSLH} t_{OSHL}	Output to Output Skew (Note 4)	2.7			1.5		1.5	ns	$C_L = 50$ pF
		3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

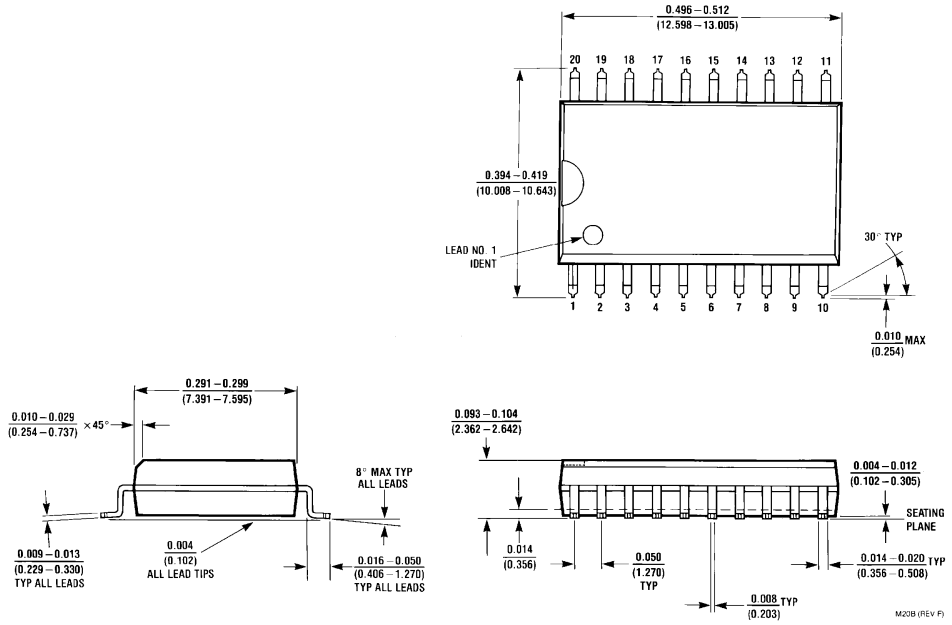
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		32				pF

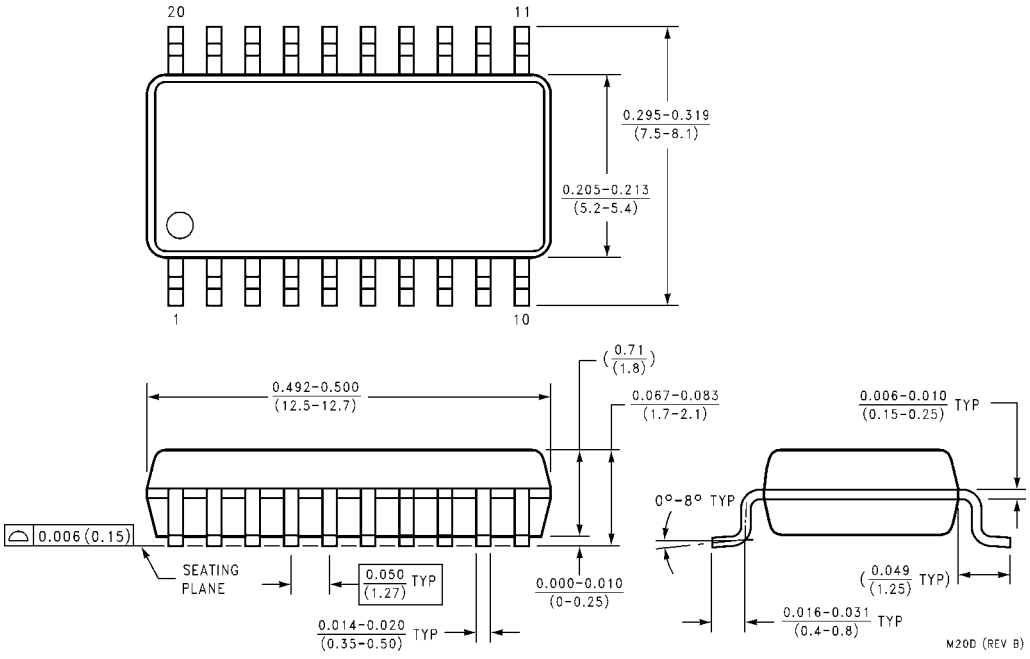
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per F/F)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

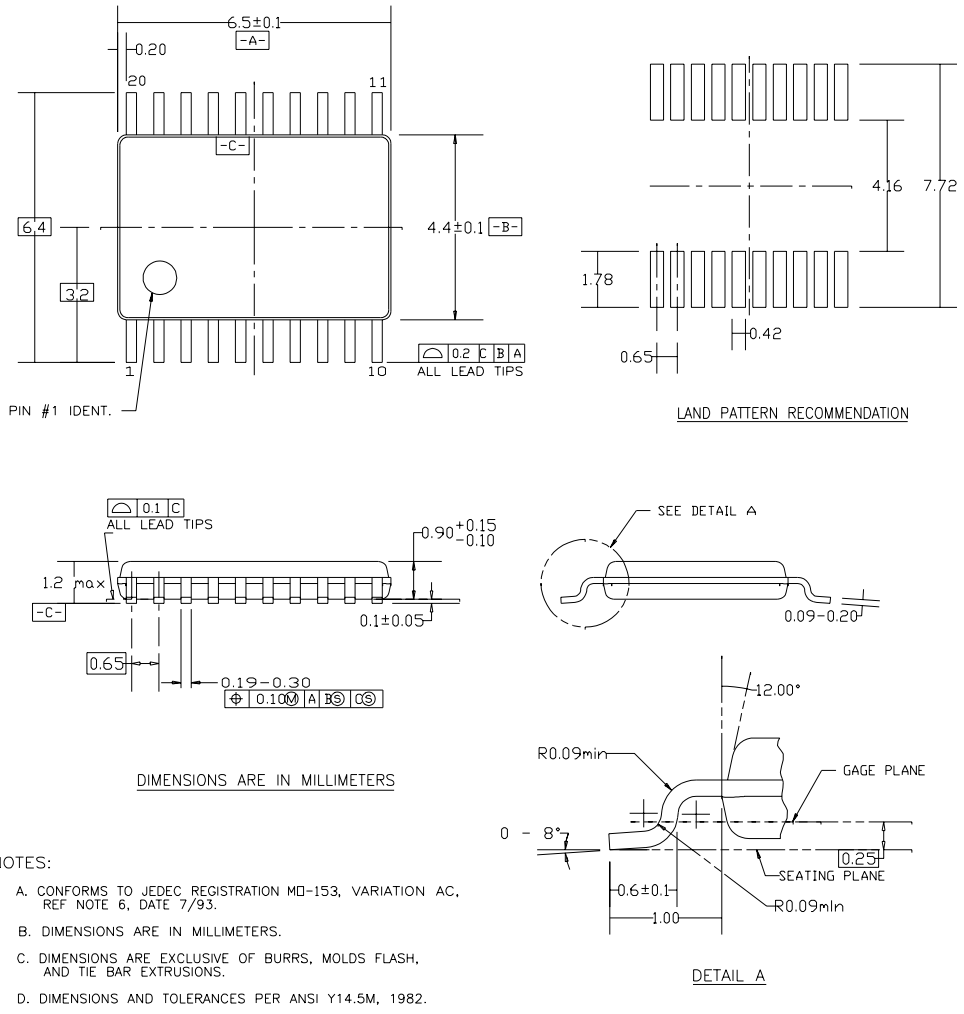


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP) EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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National Semiconductor

February 1996

74LVX3L384
10-Bit Low Power Bus Switch

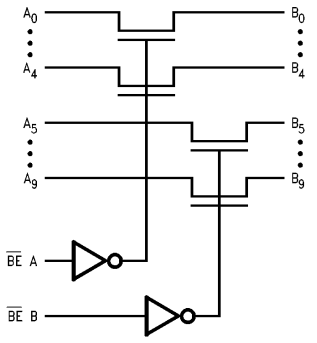
General Description

The LVX3L384 provides 10 bits of high-speed CMOS TTL-compatible bus switches. The low on resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise. The device is organized as two 5-bit switches with separate bus enable ($\overline{BE}$) signals. When $\overline{BE}$ is low, the switch is on and port A is connected to port B. When $\overline{BE}$ is high, the switch is open and a high-impedance state exists between the two ports.

Features

- 5Ω switch connection between two ports
- Zero propagation delay
- Ultra low power with 0.2 μA typical I_{CC}
- Zero ground bounce in flow-through mode
- Control inputs compatible with TTL level
- Available in SOIC, TSSOP and QSOP (SSOP 0.15″ Body width)

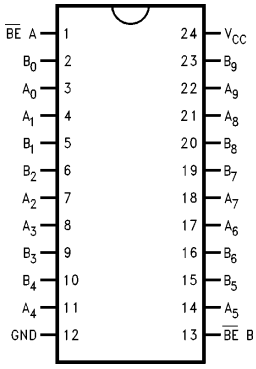
Logic Diagram



TL/F/11653–1

Connection Diagram

Pin Assignment for SOIC, QSOP and TSSOP



TL/F/11653–2

Truth Table

$\overline{BE}$ A	$\overline{BE}$ B	B_0–B_4	B_5–B_9	Function
L	L	A_0–A_4	A_5–A_9	Connect
L	H	A_0–A_4	HIGH-Z State	Connect
H	L	HIGH-Z State	A_5–A_9	Connect
H	H	HIGH-Z State	HIGH-Z State	Disconnect

Pin Names	Description
$\overline{BE}$ A, $\overline{BE}$ B	Bus Switch Enable
A_0–A_9	Bus A
B_0–B_9	Bus B

	SOIC JEDEC	QSOP	TSSOP
Order Number	74LVX3L384WM 74LVX3L384WMX	74LVX3L384QSC 74LVX3L384QSCX	74LVX3L384MTC 74LVX3L384MTCX
See NS Package Number	M24B	MQA24	MTC24

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Switch Voltage (V_S)	−0.5 to +7.0V
DC Input Input Voltage (V_I) (Note 2)	−0.5 to +7.0V
DC Input Diode Current with ($V_I < 0$)	−20 mA
DC Output (I_O) Sink Current	120 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation	0.5W

Note 1: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Note 2: *The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.*

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.0V to 5.5V
Free Air Operating Temperature (T_A)	−40°C to +85°C

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	74LVX3L384 $T_A = -40°C$ to $+85°C$			Units	Conditions
			Min	Typ (Note 5)	Max		
V_{IK}	Maximum Clamp Diode Voltage	4.75			−1.2	V	$I_{IN} = -18$ mA
V_{IH}	Minimum High Level Input Voltage	4.75–5.25	2.0			V	
V_{IL}	Maximum Low Level Input Voltage	4.75–5.25			0.8	V	
I_{IN}	Maximum Input Leakage Current	0			10	μA	$0 \le V_{IN} \le 5.25V$
		5.25			±1	μA	
I_{OZ}	Maximum TRI-STATE® I/O Leakage	5.25			±10	μA	$0 \le A, B \le V_{CC}$
I_{OS}	Short Circuit Current	4.75	100			mA	$V_I(A), V_I(B) = 0V$, $V_I(B), V_I(A) = 4.75V$
R_{ON}	Switch On Resistance (Note 3)	4.75		5	7	Ω	$V_I = 0V$, $I_{ON} = 30$ mA
				10	15	Ω	$V_I = 2.4V$, $I_{ON} = 15$ mA
I_{CC}	Maximum Quiescent Supply Current	5.25		0.2	10	μA	$V_I = V_{CC}$, GND $I_O = 0$
ΔI_{CC}	Increase in I_{CC} per Input (Note 4)	5.25			2.5	mA	$V_{IN} = 3.15V$, $I_O = 0$ Per Control Input

Note 3: Measured by voltage drop between A and B pin at indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 4: Per TTL driven Input ($V_{IN} = 3.15V$, control inputs only). A and B pins do not contribute to I_{CC}.

Note 5: All typical values are at $V_{CC} = 5.0V$, $T_A = 25°C$.

AC Electrical Characteristics:

Symbol	Parameter	V_{CC} (V)	74LVX3L384 $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF			Units
			Min	Typ (Note 5)	Max	
T_{PLH} T_{PHL}	Data Propagation Delay An to Bn or Bn to An (Note 6)	4.75			0.25	ns
T_{PZL} T_{PZH}	Switch Enable Time $\overline{BE}_A$, $\overline{BE}_B$ to An, Bn	4.75	1.5		6.5	ns
T_{PLZ} T_{PHZ}	Switch Disable Time $\overline{BE}_A$, $\overline{BE}_B$ to An, Bn	4.75	1.5		5.5	ns

Note 5: All typical values are at $V_{CC} = 5.0V$, $T_A = 25°C$.

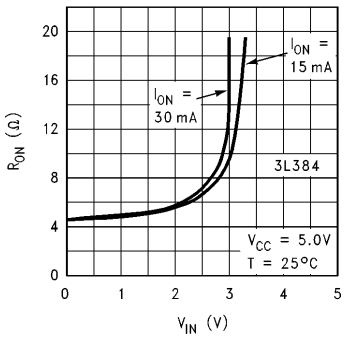
Note 6: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On resistance of the switch and the load capacitance. The time constant for the switch and alone is of the order of 0.25 ns for 50 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Capacitance (Note)

Symbol	Parameter	Typ	Max	Units	Conditions
C_{IN}	Control Input Capacitance	4	6	pF	$V_{CC} = 5.0V$
$C_{I/O}$ (OFF)	Input/Output Capacitance	9	13	pF	$V_{CC} = 5.0V$

Note: Capacitance is characterized but not tested.

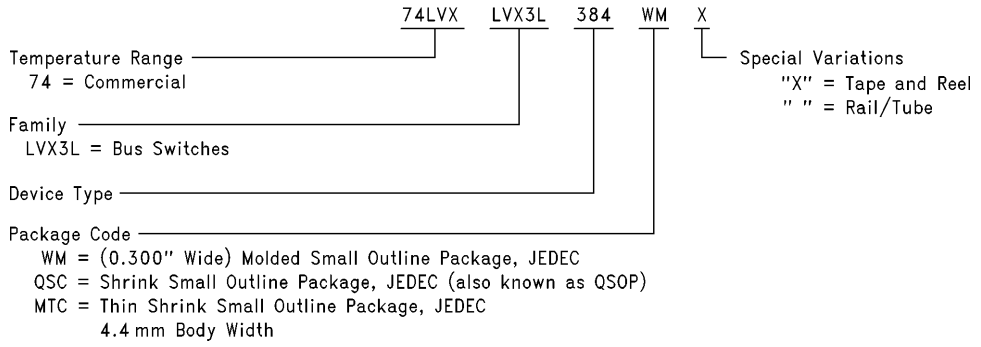
74LVX3L384 V_{IN} vs R_{ON} (Typ)



TL/F/11653–3

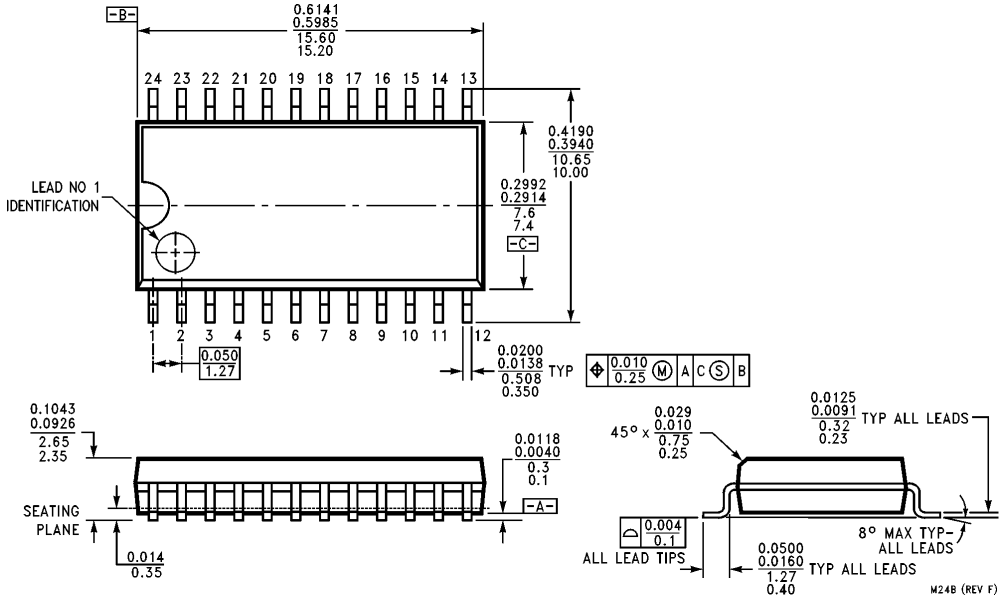
74LVX3L384 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



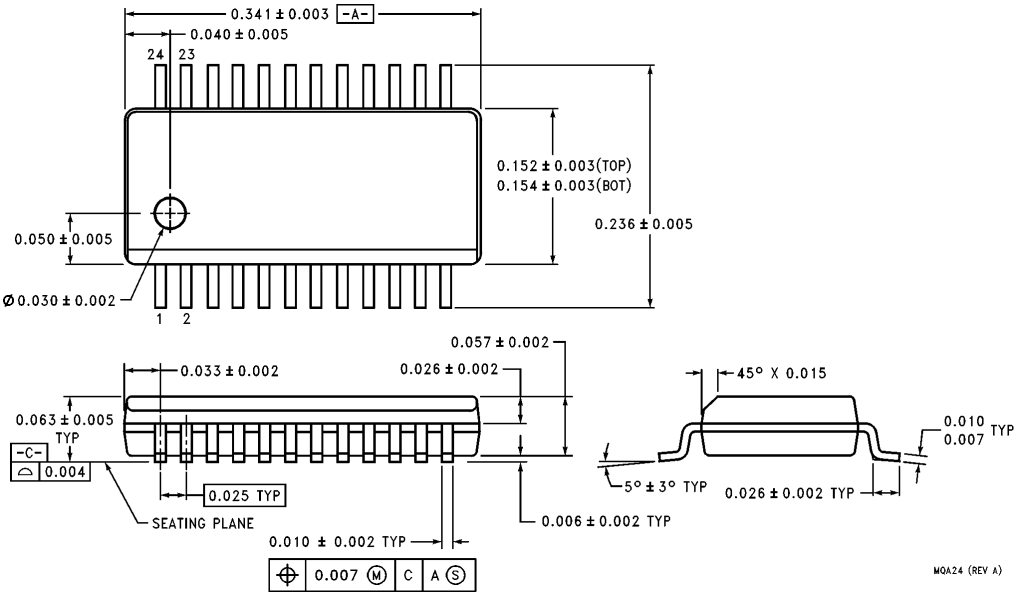
TL/F/11653–4

Physical Dimensions inches / millimeters



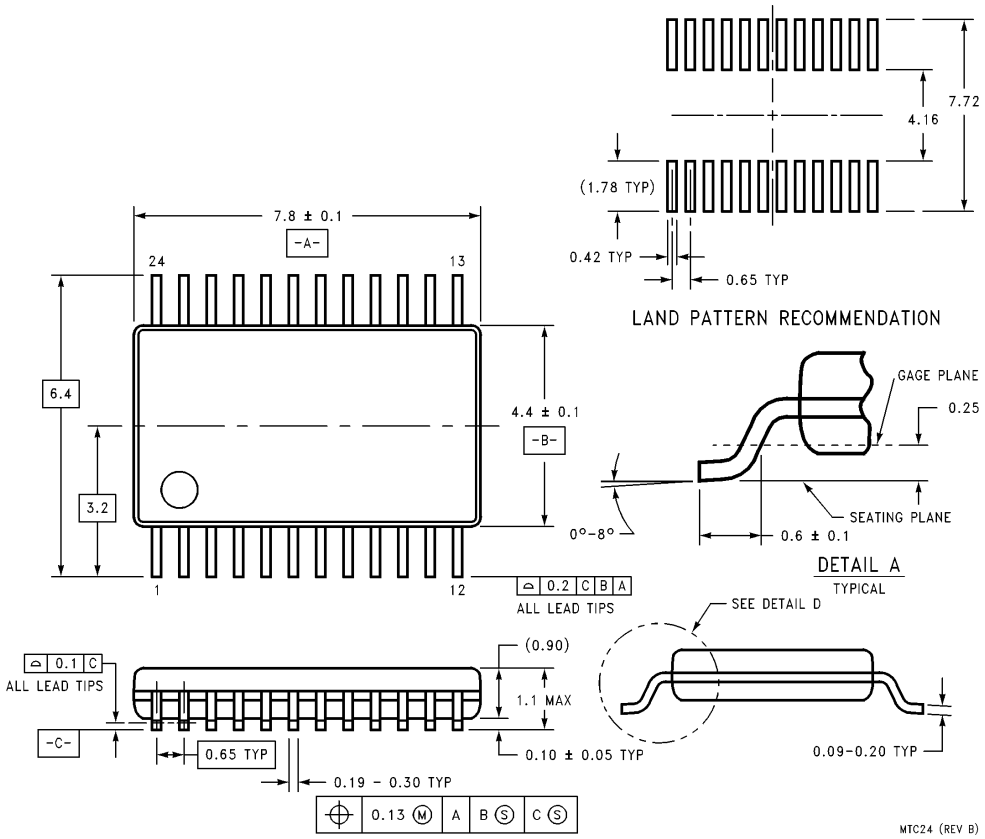
24-Lead (0.300" Wide) Small Outline Package, JEDEC
Order Number 74LVX3L384WM or 74LVX3L384WMX
NS Package Number M24B

Physical Dimensions inches (Continued)



24-Lead (0.150″ Wide) Shrink Small Outline Package, JEDEC (QSC)
(also known as QSOP)
Order Number 74LVX3L384QSC or 74LVX3L384QSCX
NS Package Number MQA24

Physical Dimensions inches (Continued)



24-Lead Thin Shrink Small Outline Package, JEDEC
Order Number 74LVX3L384MTC or 74LVX3L384MTCX
NS Package Number MTC24

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

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74LVX4245
8-Bit Dual Supply Translating Transceiver with 3-STATE Outputs

General Description

The LVX4245 is a dual-supply, 8-bit translating transceiver that is designed to interface between a 5V bus and a 3V bus in a mixed 3V/5V supply environment. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a high impedance condition. The A Port interfaces with the 5V bus; the B Port interfaces with the 3V bus.

The LVX4245 is suitable for mixed voltage applications such as laptop computers using 3.3V CPU's and 5V LCD displays.

Features

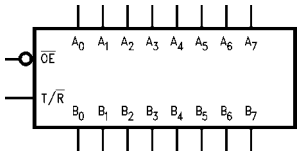
- Bidirectional interface between 5V and 3V buses
- Control inputs compatible with TTL level
- 5V data flow at A Port and 3V data flow at B Port
- Outputs source/sink 24 mA at 5V bus; 12 mA at 3V bus
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Implements patented EMI reduction circuitry
- Functionally compatible with the 74 series 245

Ordering Code:

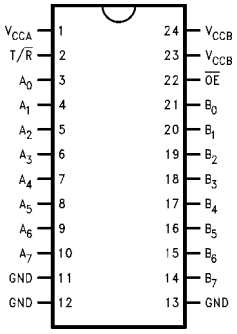
Order Number	Package Number	Package Description
74LVX4245WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX4245QSC	MQA24	24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74LVX4245MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

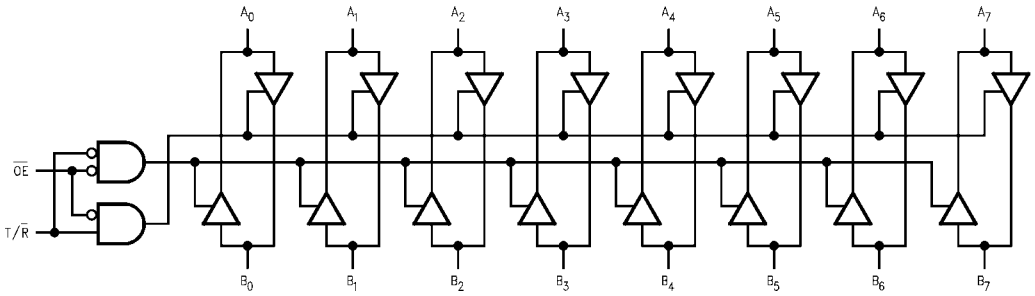
Pin Names	Description
$\overline{OE}$	Output Enable Input
$T/\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CCA}, V_{CCB})	−0.5V to +7.0V
DC Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	−0.5V to V_{CCA} + 0.5V
DC Input/Output Voltage ($V_{I/O}$)	
@ A_n	−0.5V to V_{CCA} + 0.5V
@B_n	−0.5V to V_{CCB} + 0.5V
DC Input Diode Current (I_{IN})	
@ $\overline{OE}$, T/$\overline{R}$	±20 mA
DC Output Diode Current (I_{OK})	±50 mA
DC Output Source or Sink Current	
(I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
and Max Current @ I_{CCA}	±200 mA
@ I_{CCB}	±100 mA
Storage Temperature Range	
(T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage	
V_{CCA}	4.5V to 5.5V
V_{CCB}	2.7V to 3.6V
Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	0V to V_{CCA}
Input/Output Voltage ($V_{I/O}$)	
@ A_n	0V to V_{CCA}
@ B_n	0V to V_{CCB}
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	8 ns/V
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must he held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	T_A +25°C	T_A = −40°C to +85°C		Units	Conditions
					Typ	Guaranteed Limits			
V_{IHA}	Minimum	A_n, T/$\overline{R}$,	5.5	3.3		2.0	2.0	V	V_{OUT} ≤ 0.1V or
	HIGH Level	$\overline{OE}$	4.5	3.3		2.0	2.0		≥ V_{CC} − 0.1V
V_{IHB}	Input Voltage	B_n	5.0	3.6		2.0	2.0		
			5.0	2.7		2.0	2.0		
V_{ILA}	Maximum	A_n, T/$\overline{R}$,	5.5	3.3		0.8	0.8	V	V_{OUT} ≤ 0.1V or
	LOW Level	$\overline{OE}$	4.5	3.3		0.8	0.8		≥ V_{CC} −0.1V
V_{ILB}	Input Voltage	B_n	5.0	2.7		0.8	0.8		
			5.0	3.6		0.8	0.8		
V_{OHA}	Minimum HIGH Level		4.5	3.0	4.5	4.4	4.4	V	I_{OUT} = −100 µA
	Output Voltage		4.5	3.0	4.25	3.86	3.76		I_{OH} = −24 mA
V_{OHB}			4.5	3.0	2.99	2.9	2.9	V	I_{OUT} = −100 µA
			4.5	3.0	2.8	2.4	2.4		I_{OH} = −12 mA
			4.5	2.7	2.5	2.4	2.4		I_{OL} = −8 mA
V_{OLA}	Maximum LOW Level		4.5	3.0	0.002	0.1	0.1	V	I_{OUT} =100 µA
	Output Voltage		4.5	3.0	0.18	0.36	0.44		I_{OL} = 24 mA
V_{OLB}			4.5	3.0	0.002	0.1	0.1		I_{OUT} = 100 µA
			4.5	3.0	0.1	0.31	0.4	V	I_{OL} = 12 mA
			4.5	2.7	0.1	0.31	0.4		I_{OL} = 8 mA
I_{IN}	Maximum Input								V_I = V_{CCA}, GND
	Leakage Current		5.5	3.6		±0.1	±1.0	µA	
	@ $\overline{OE}$, T/$\overline{R}$								
I_{OZA}	Maximum 3-STATE								V_I = V_{IL}, V_{IH}
	Output Leakage		5.5	3.6		±0.5	±5.0	µA	$\overline{OE}$ = V_{CCA}
	@ A_n								V_O = V_{CCA}, GND
I_{OZB}	Maximum 3-STATE								V_I = V_{IL}, V_{IH}
	Output Leakage		5.5	3.6		±0.5	±5.0	µA	$\overline{OE}$ = V_{CCA}
	@ B_n								V_O = V_{CCB}, GND

DC Electrical Characteristics (Continued)

Symbol	Parameter	V_{CCA} (V)	V_{CCB} (V)	T_A +25°C	T_A = −40°C to +85°C		Units	Conditions
				Typ	Guaranteed Limits			
ΔI_{CC}	Maximum I_{CCT}/Input @ A_n, T/$\overline{R}$, $\overline{OE}$	5.5	3.6	1.0	1.35	1.5	mA	$V_I = V_{CCA} - 2.1V$
	Input @ B_n	5.5	3.6		0.35	0.5	mA	$V_I = V_{CCB} - 0.6V$
I_{CCA}	Quiescent V_{CCA} Supply Current	5.5	3.6		8	80	µA	$A_n = V_{CCA}$ or GND $B_n = V_{CCB}$ or GND, $\overline{OE}$ = GND T/$\overline{R}$ = GND
I_{CCB}	Quiescent V_{CCB} Supply Current	5.5	3.6		5	50	µA	$A_n = V_{CCA}$ or GND $B_n = V_{CCB}$ or GND, $\overline{OE}$ = GND T/$\overline{R}$ = V_{CCA}
V_{OLPA}	Quiet Output Maximum	5.0	3.3		1.5		V	(Note 4)(Note 5)
V_{OLPB}	Dynamic V_{OL}	5.0	3.3		0.8			
V_{OLVA}	Quiet Output Minimum	5.0	3.3		−1.2		V	(Note 4)(Note 5)
V_{OLVB}	Dynamic V_{OL}	5.0	3.3		−0.8			
V_{IHDA}	Minimum HIGH Level	5.0	3.3		2.0		V	(Note 4)(Note 6)
V_{IHDB}	Dynamic Input Voltage	5.0	3.3		2.0			
V_{ILDA}	Maximum LOW Level	5.0	3.3		0.8		V	(Note 4)(Note 6)
V_{ILDB}	Dynamic Input Voltage	5.0	3.3		0.8			

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Worst case package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to V_{CC} level; one output at GND.

Note 6: Max number of Data Inputs (n) switching. (n–1) inputs switching 0V to V_{CC} level. Input-under-test switching: V_{CC} level to threshold (V_{IHD}), OV to threshold (V_{ILD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameters	T_A = +25°C, C_L = 50 pF, V_{CCA} = 5V (Note 7), V_{CCB} = 3.3V (Note 8)			T_A = −40°C to +85°C, C_L = 50 pF, V_{CCA} = 5V (Note 7), V_{CCB} = 3.3V (Note 8)		T_A = −40°C to +85°C, C_L = 50 pF, V_{CCA} = 5V (Note 7), V_{CCB} = 2.7V		Units
		Min	Typ	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.0	5.1	8.5	1.0	9.0	1.0	10.0	ns
t_{PLH}	A to B	1.0	5.3	8.5	1.0	9.0	1.0	10.0	
t_{PHL}	Propagation Delay	1.0	5.4	8.5	1.0	9.0	1.0	10.0	ns
t_{PLH}	B to A	1.0	5.5	8.5	1.0	9.0	1.0	10.0	
t_{PZL}	Output Enable Time	1.0	6.5	10.0	1.0	10.5	1.0	11.5	ns
t_{PZH}	$\overline{OE}$ to B	1.0	6.7	10.0	1.0	10.5	1.0	11.5	
t_{PZL}	Output Enable Time	1.0	5.2	9.0	1.0	9.5	1.0	10.0	ns
t_{PZH}	$\overline{OE}$ to A	1.0	5.8	9.0	1.0	9.5	1.0	10.0	
t_{PHZ}	Output Disable Time	1.0	6.0	9.5	1.0	10.0	1.0	10.0	ns
t_{PLZ}	$\overline{OE}$ to B	1.0	3.3	6.5	1.0	7.0	1.0	7.5	
t_{PHZ}	Output Disable Time	1.0	3.9	7.0	1.0	7.5	1.0	7.5	ns
t_{PLZ}	$\overline{OE}$ to A	1.0	2.9	6.5	1.0	7.0	1.0	7.5	
t_{OSHL}	Output to Output								
t_{OSLH}	Skew (Note 9)		1.0	1.5		1.5		1.5	ns
	Data to Output								

Note 7: Voltage Range 5.0V is 5.0V ±0.5V.

Note 8: Voltage Range 3.3V is 3.3V ±0.3V.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

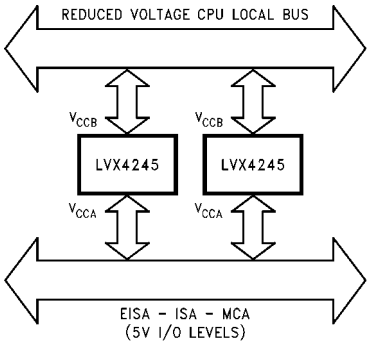
Symbol	Parameter		Typ	Units	Conditions
C_{IN}	Input Capacitance		4.5	pF	V_{CC} = Open
$C_{I/O}$	Input/Output Capacitance		15	pF	V_{CCA} = 5.0V V_{CCB} = 3.3V
C_{PD}	Power Dissipation Capacitance (Note 10)	B→A	55	pF	V_{CCA} = 5.0V V_{CCB} = 3.3V
		A→B	40	pF	

Note 10: C_{PD} is measured at 10 MHz

8-Bit Dual Supply Translating Transceiver

The LVX4245 is a dual supply device capable of bidirectional signal translation. This level shifting ability provides an efficient interface between low voltage CPU local bus with memory and a standard bus defined by 5V I/O levels. The device control inputs can be controlled by either the low voltage CPU and core logic or a bus arbitrator with 5V I/O levels.

Manufactured on a sub-micron CMOS process, the LVX4245 is ideal for mixed voltage applications such as notebook computers using 3.3V CPU's and 5V peripheral devices.



Power Up Considerations

To insure the system does not experience unnecessary I_{CC} current draw, bus contention, or oscillations during power up, the following guidelines should be adhered to (refer to Table 1):

- Power up the control side of the device first. This is the V_{CCA}.
- $\overline{OE}$ should ramp with or ahead of V_{CCA}. This will help guard against bus contention.
- The Transmit/Receive control pin (T/$\overline{R}$) should ramp with or ahead of V_{CCA}, this will ensure that the A Port data pins are configured as inputs. With V_{CCA} receiving power first, the A I/O Port should be configured as inputs to help guard against bus contention and oscillations.
- A side data inputs should be driven to a valid logic level. This will prevent excessive current draw.

The above steps will ensure that no bus contention or oscillations, and therefore no excessive current draw occurs during the power up cycling of these devices. These steps will help prevent possible damage to the translator devices and potential damage to other system components.

TABLE 1. Low Voltage Translator Power Up Sequencing Table

Device Type	V_{CCA}	V_{CCB}	T/$\overline{R}$	$\overline{OE}$	A Side I/O	B Side I/O	Floatable Pin Allowed
74LVX4245	5V (power up 1st)	3V (power up 2nd)	ramp with V_{CCA}	ramp with V_{CCA}	logic 0V or V_{CCA}	outputs	No

Please reference Application Note AN-5001 for more detailed information on using Fairchild's LVX Low Voltage Dual Supply CMOS Translating Transceivers.

Applications: Mixed Mode Dual Supply Interface Solution

LVX4245 is designed to solve 3V/5V interfacing issues when CMOS devices cannot tolerate I/O levels above their applied V_{CC}. If an I/O pin of 3V ICs is driven by 5V ICs, the P-Channel transistor in 3V ICs will conduct causing current flow from I/O bus to the 3V power supply. The resulting high current flow can cause destruction of 3V ICs through latchup effects. To prevent this problem, a current limiting resistor is used typically under direct connection of 3V ICs and 5V ICs, but it causes speed degradation.

In a better solution, the LVX4245 configures two different output levels to handle the dual supply interface issues. The “A” port is a dedicated 5V port to interface 5V ICs. The “B” port is a dedicated port to interface 3V ICs. *Figure 2* shows how LVX4245 fits into a system with 3V subsystem and 5V subsystem.

This device is also configured as an 8-bit 245 transceiver, giving the designer 3-STATE capabilities and the ability to select either bidirectional or unidirectional modes. Since the center 20 pins are also pin compatible to 74 series 245, as shown in *Figure 1*, the designer could use this device in either a 3V system or a 5V system without any further work to re-layout the board.

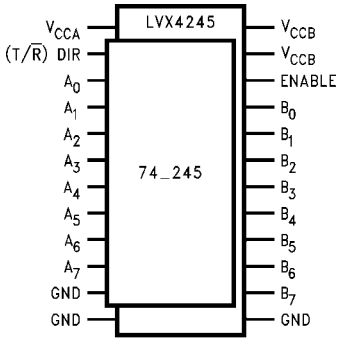


FIGURE 1. LVX4245 Pin Arrangement is Compatible to 20-Pin 74 Series 245

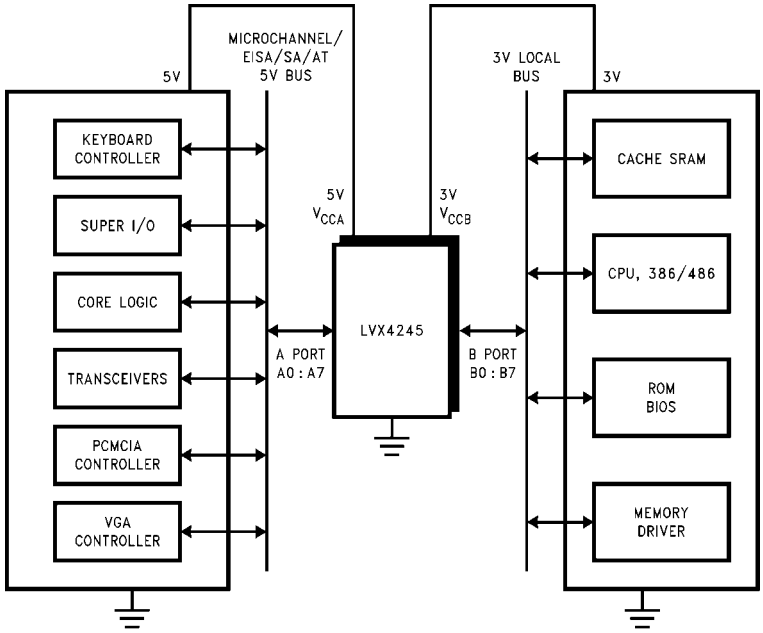
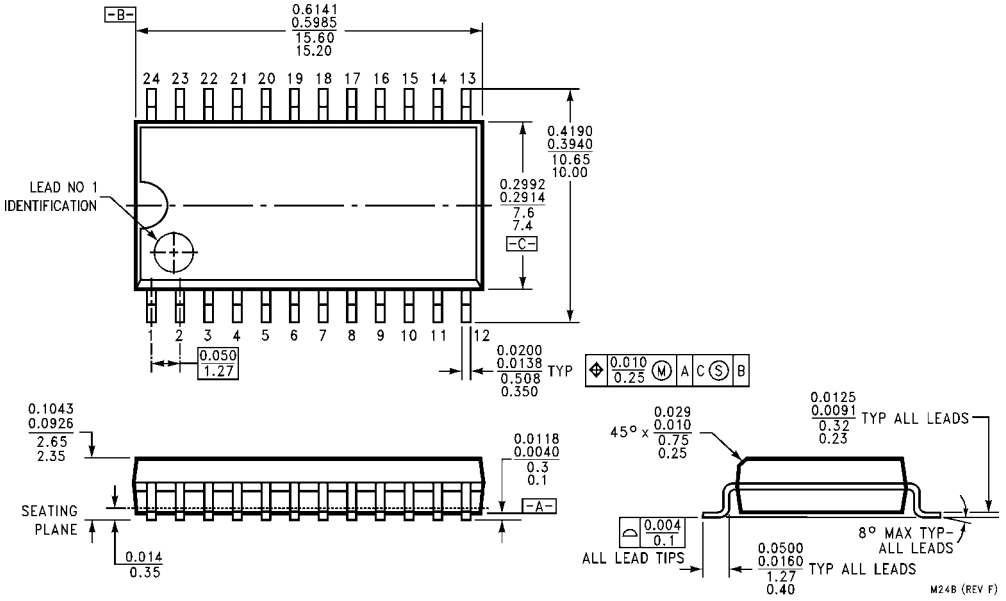
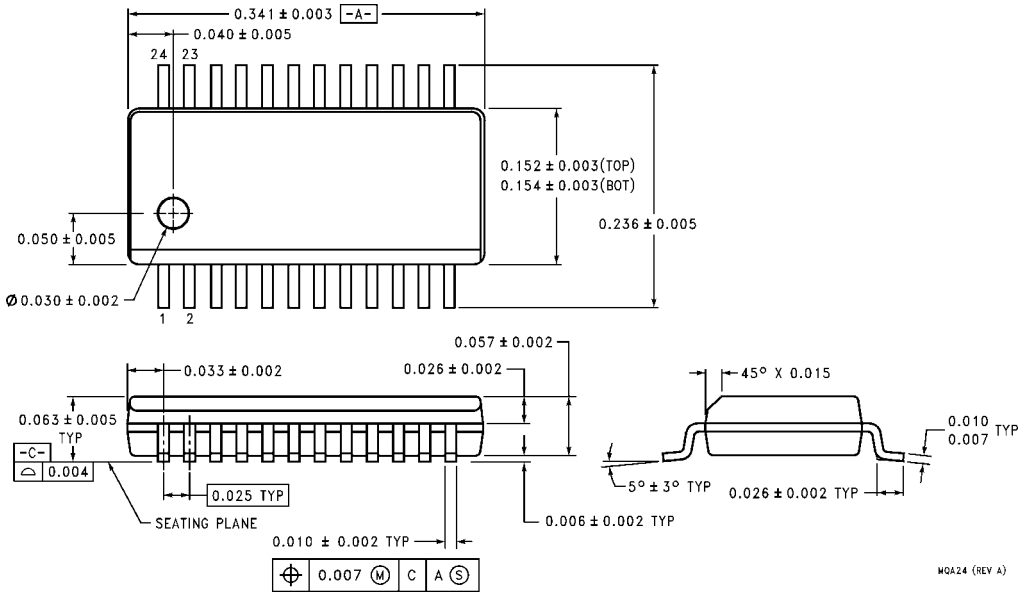


FIGURE 2. LVX4245 Fits into a System with 3V Subsystem and 5V Subsystem

Physical Dimensions inches (millimeters) unless otherwise noted

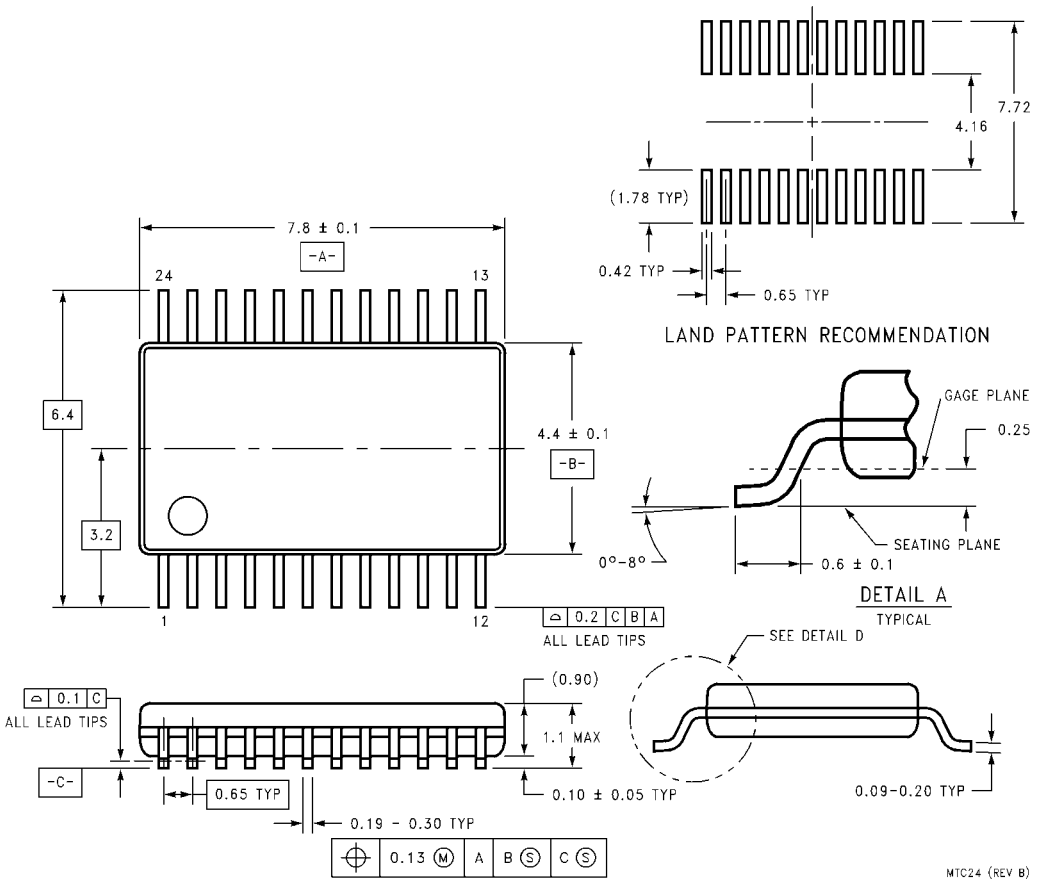


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

September 1999
Revised September 1999

74LVX541
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVX541 is an octal non-inverting buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

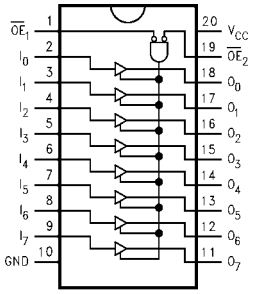
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

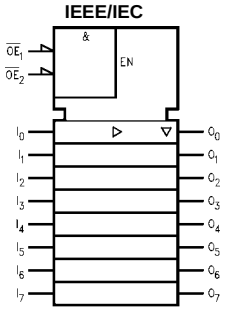
Order Number	Package Number	Package Description
74LVX541M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVX541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names	Descriptions
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0 - I_7	Inputs
O_0 - O_7	3-STATE Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +3.6V
Input Voltage (V_I)	0V to +5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input	2.0	1.5			1.5				
	Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level Input	2.0			0.5		0.5			
	Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output	2.0	1.9	2.0		1.9				I_{OH} = −50 μA
	Voltage	3.0	2.9	3.0		2.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output	2.0		0.0	0.1		0.1			I_{OL} = 50 μA
	Voltage	3.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output OFF-State Current	3.6			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	C_L = 50 pF
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	C_L = 50 pF
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	C_L = 50 pF
V_{ILD}	Maximum HIGH Level Dynamic Input Voltage	3.3		0.8	V	C_L = 50 pF

Note 3: Input t_r = t_f = 3 ns.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	2.7		6.1	11.3	1.0	13.5	ns	$C_L = 15$ pF
t_{PHL}	Time			8.6	14.9	1.0	17.0		$C_L = 50$ pF
		3.3 ± 0.3		4.7	7.0	1.0	8.5		$C_L = 15$ pF
				7.2	10.5	1.0	12.0		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		7.1	13.8	1.0	16.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			9.6	17.3	1.0	20.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		6.8	10.5	1.0	12.5		$C_L = 15$ pF, $R_L = 1$ kΩ
				9.3	14.0	1.0	16.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		11.6	17.9	1.0	20.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		10.7	15.4	1.0	17.5		
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$; $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.

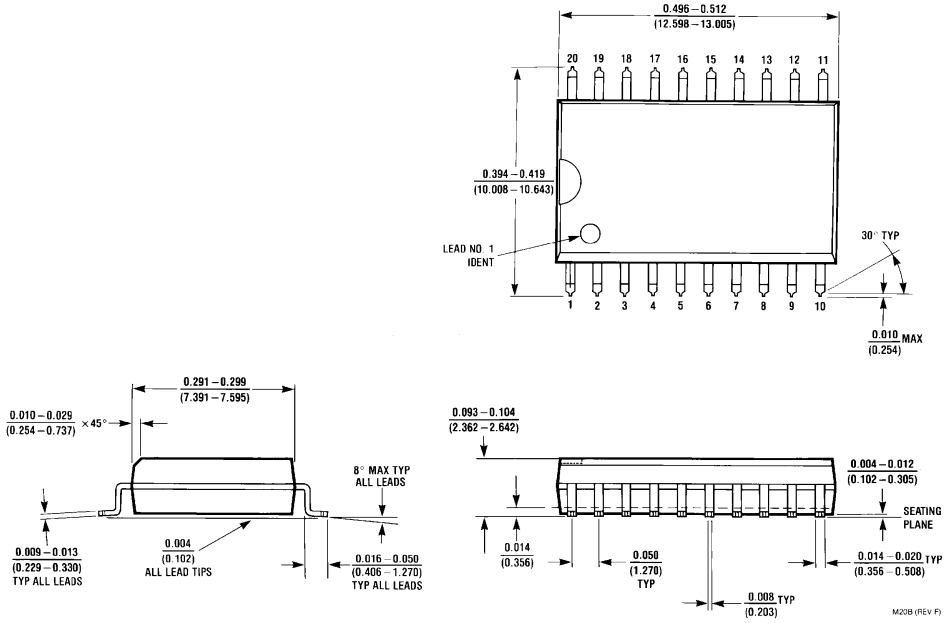
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		19				pF

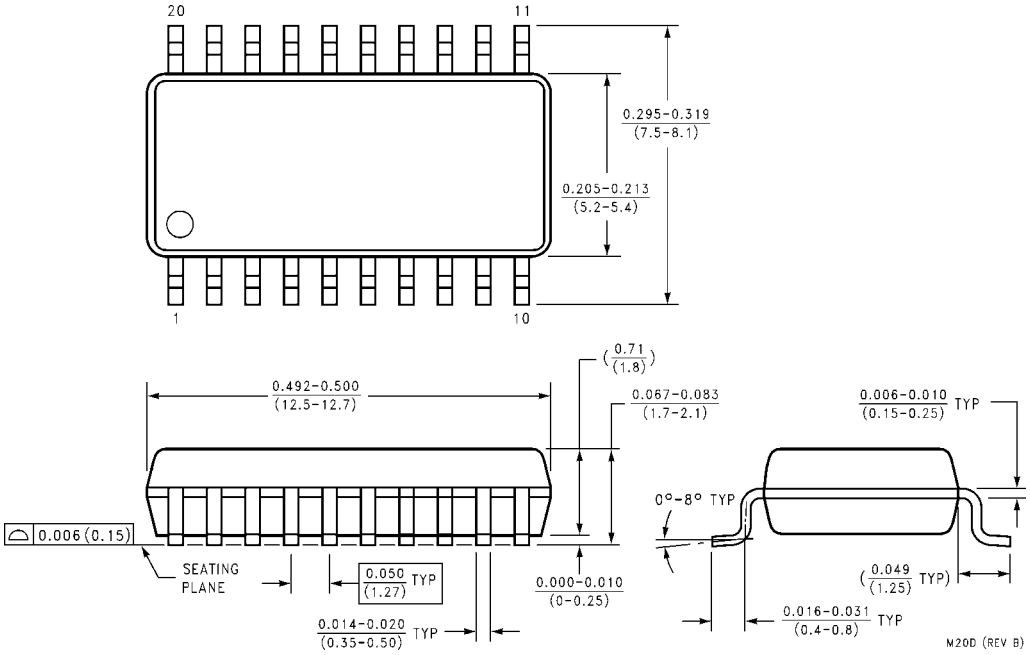
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \dfrac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per bit)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

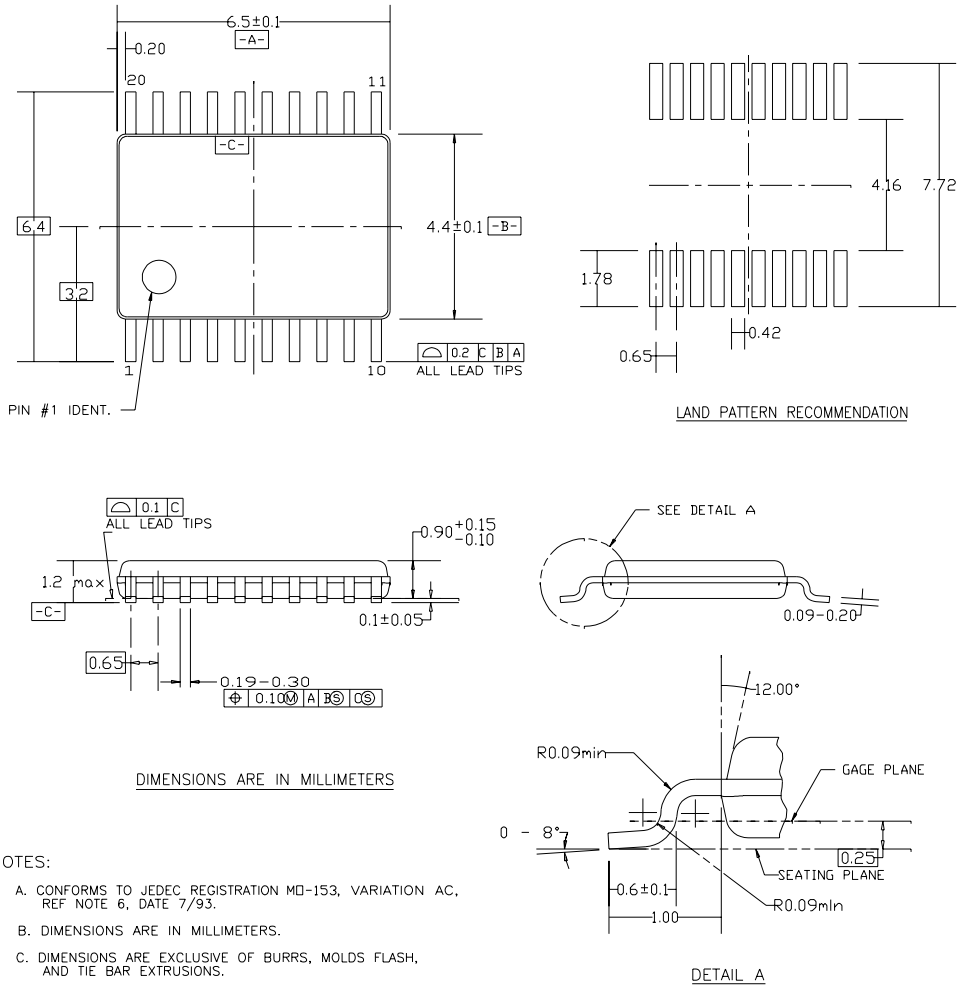


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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June 1993
Revised March 1999

74LVX573
Low Voltage Octal Latch with 3-STATE Outputs

General Description

The LVX573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs. The LVX573 is functionally identical to the LVX373 but with inputs and outputs on opposite sides of the package. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

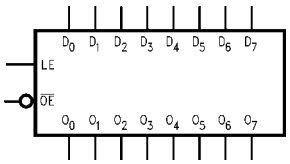
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

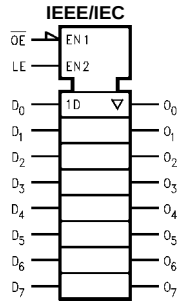
Ordering Code:

Order Number	Package Number	Package Description
74LVX573M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

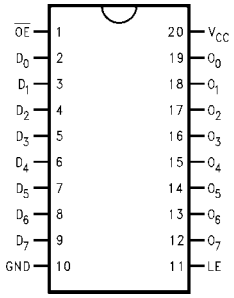
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Functional Description

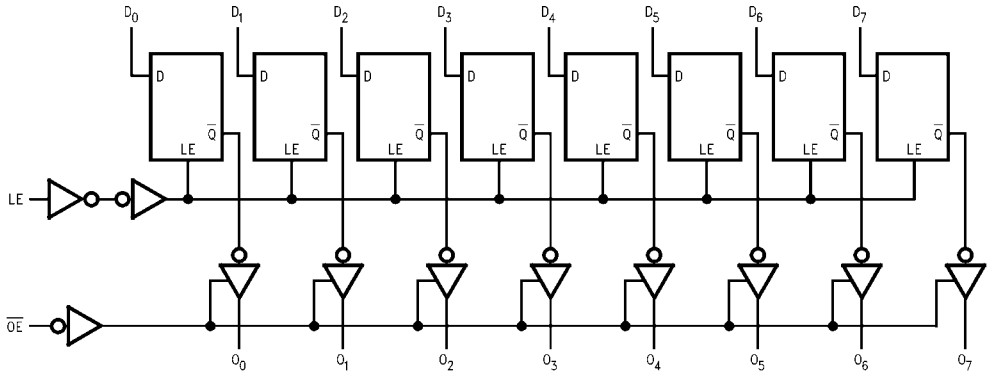
The LVX573 contains eight D-type latches. When the enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage
L = LOW Voltage
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output	3.6			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: (Input t_r = t_f = 3ns)

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		7.6	14.5	1.0	17.5	ns	$C_L = 15$ pF
t_{PHL}	Delay Time			10.1	18.0	1.0	21.0		$C_L = 50$ pF
	D_n to O_n	3.3 ± 0.3		5.9	9.3	1.0	11.0		$C_L = 15$ pF
				8.4	12.8	1.0	14.5		$C_L = 50$ pF
t_{PLH}	Propagation	2.7		8.2	15.6	1.0	18.5	ns	$C_L = 15$ pF
t_{PHL}	Delay Time			10.7	19.1	1.0	22.0		$C_L = 50$ pF
	LE to O_n	3.3 ± 0.3		6.4	10.1	1.0	12.0		$C_L = 15$ pF
				8.9	13.6	1.0	15.5		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		7.8	15.0	1.0	18.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			10.3	18.5	1.0	22.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		6.1	9.7	1.0	12.0		$C_L = 15$ pF, $R_L = 1$ kΩ
				8.6	13.2	1.0	15.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		12.1	19.1	1.0	22.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		10.1	13.6	1.0	15.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_W	LE Pulse	2.7	6.5			7.5		ns	
	Width	3.3 ± 0.3	5.0			5.0			
t_S	Setup Time	2.7	5.0			5.0		ns	
	D_n to LE	3.3 ± 0.3	3.5			3.5			
t_H	Hold Time	2.7	1.5			1.5		ns	
	D_n to LE	3.3 ± 0.3	1.5			1.5			
t_{OSHL}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSLH}	Skew (Note 4)	2.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.

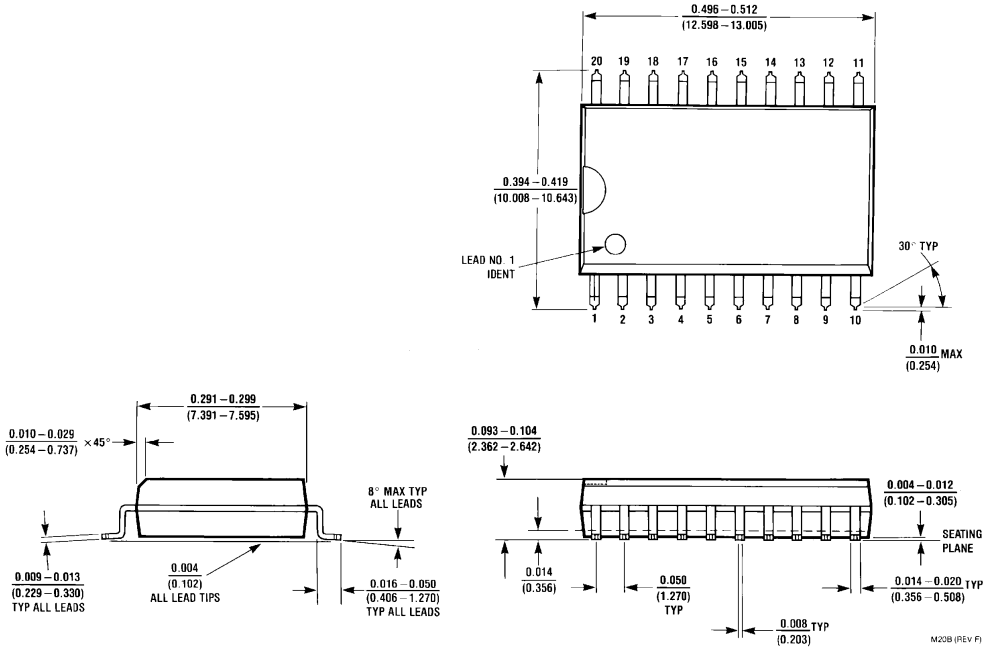
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		27				pF

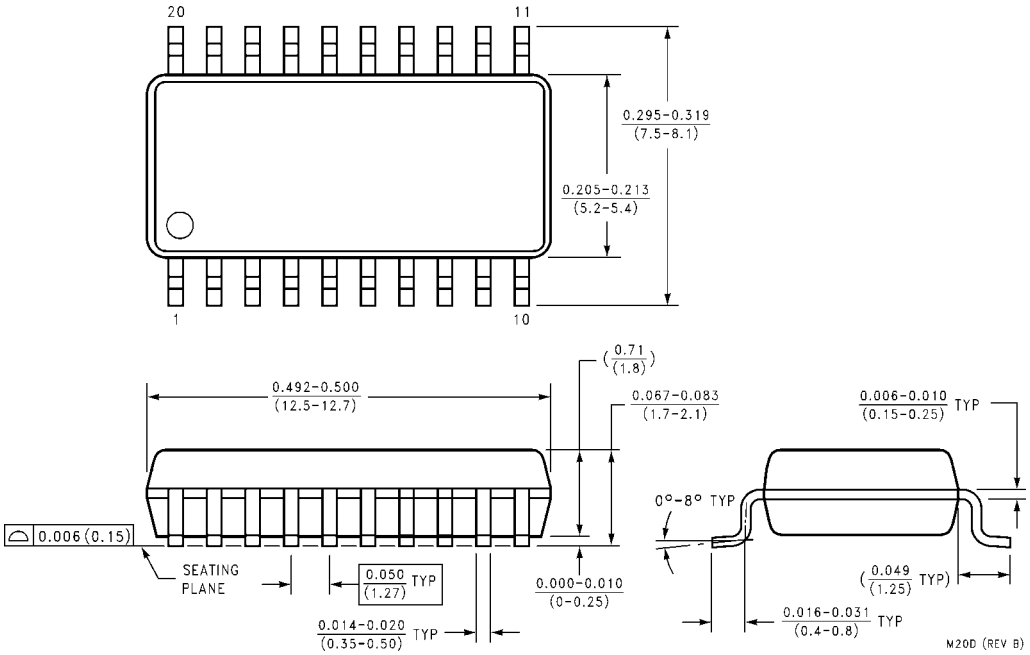
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per latch)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

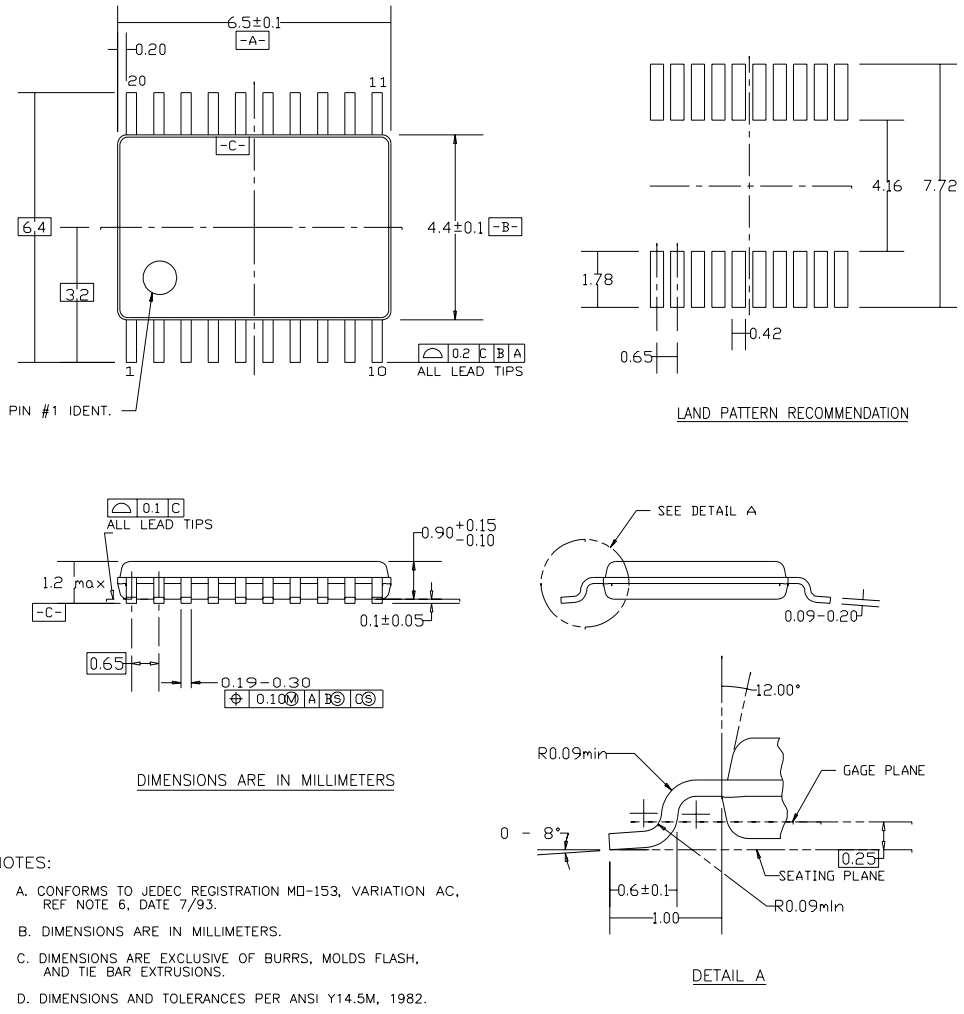


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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June 1993
Revised March 1999

74LVX574
Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVX574 is a high-speed octal D-type flip-flop which is controlled by an edge-triggered clock input (CP) and a buffered common Output Enable ($\overline{OE}$) input. When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state. The LVX574 is functionally identical to the LVX374 but with inputs and outputs on opposite sides of the package. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

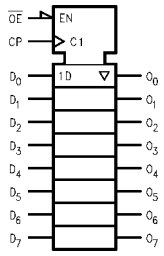
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

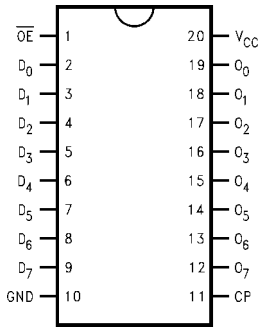
Order Number	Package Number	Package Description
74LVX574M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

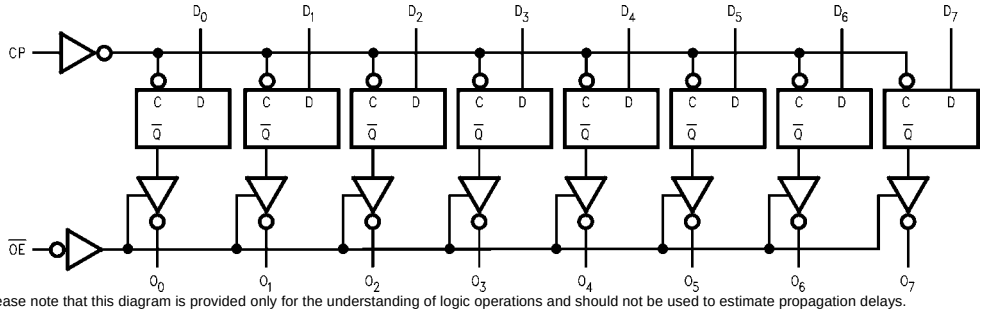
The LVX574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output	3.6			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: (Input t_r = t_f = 3 ns)

AC Electrical Characteristics (Note 4)

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum	2.7	60	115		50		MHZ	$C_L = 15$ pF
	Clock		45	60		40			$C_L = 50$ pF
	Frequency	3.3 ± 0.3	80	125		65			$C_L = 15$ pF
			50	75		45			$C_L = 50$ pF
t_{PLH}	Propagation	2.7		9.2	14.5	1.0	17.5	ns	$C_L = 15$ pF
t_{PHL}	Delay Time			11.5	18.0	1.0	21.0		$C_L = 50$ pF
	CP to O_n	3.3 ± 0.3		8.5	13.2	1.0	15.5		$C_L = 15$ pF
				11.0	16.7	1.0	19.0		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		9.8	15.0	1.0	18.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			11.4	18.5	1.0	22.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		8.2	12.8	1.0	15.0		$C_L = 15$ pF, $R_L = 1$ kΩ
				10.7	16.3	1.0	18.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		12.1	19.1	1.0	22.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		11.0	15.0	1.0	17.0		$C_L = 50$ pF, $R_L = 1$ kΩ
t_W	CP Pulse	2.7	6.5			7.5		ns	
	Width	3.3 ± 0.3	5.0			5.0			
t_S	Setup Time	2.7	5.0			5.0		ns	
	D_n to CP	3.3 ± 0.3	3.5			3.5			
t_H	Hold Time	2.7	1.5			1.5		ns	
	D_n to CP	3.3 ± 0.3	1.5			1.5			
t_{OSHL}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSLH}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.

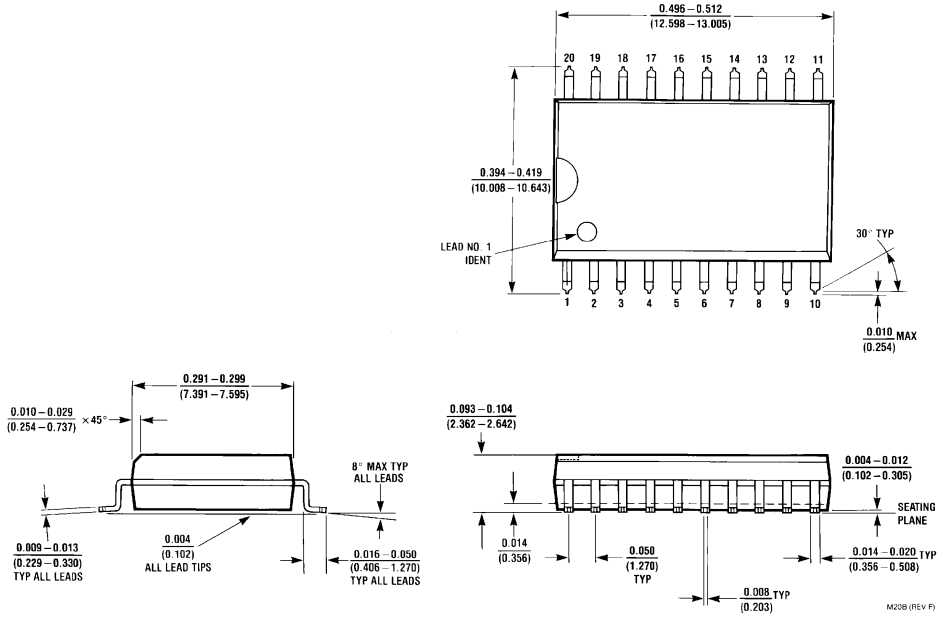
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		27				pF

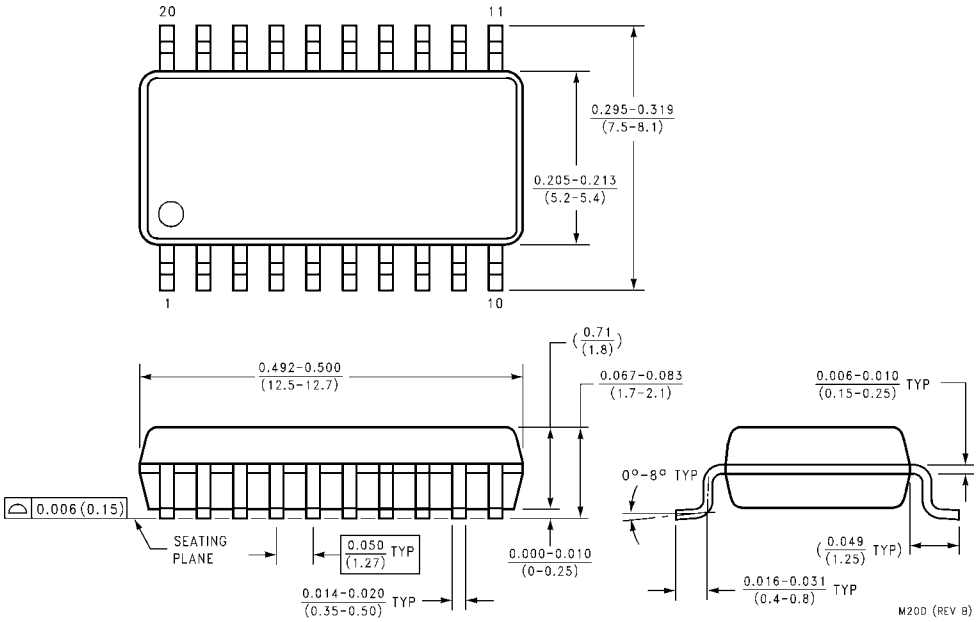
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per latch)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

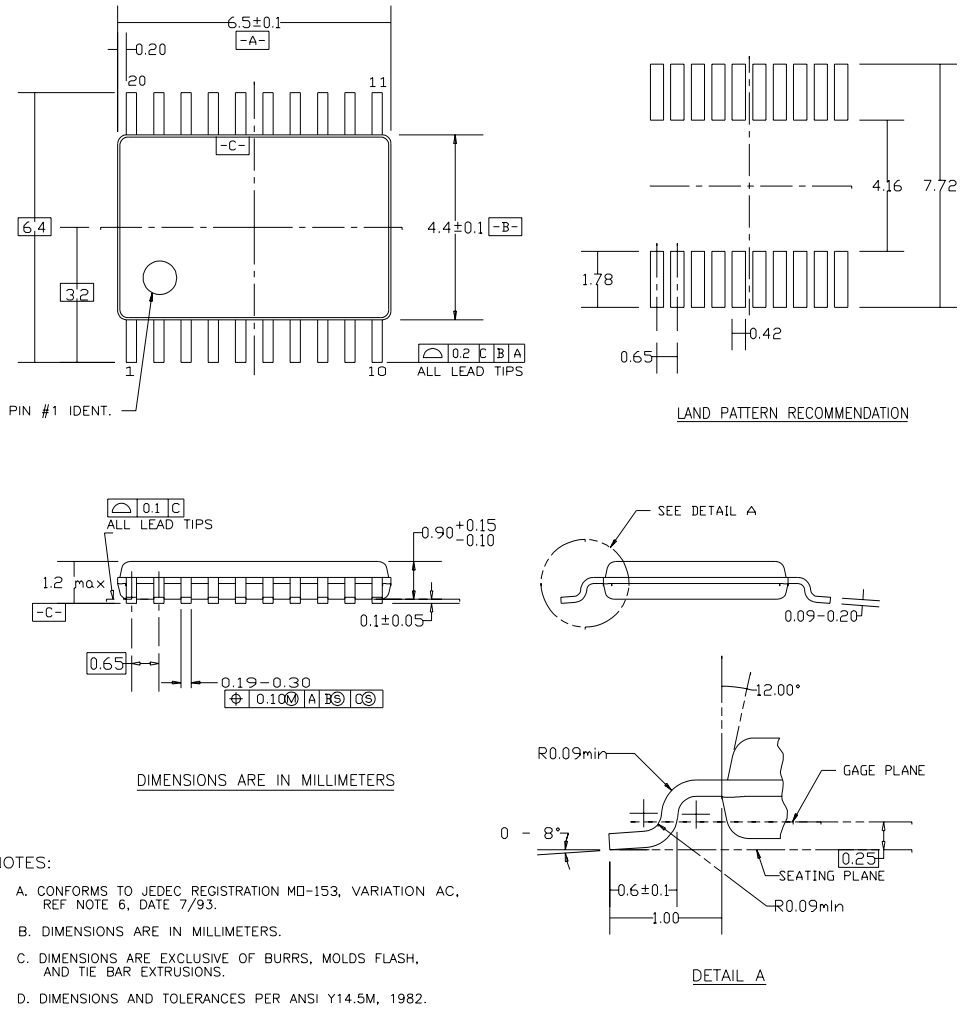


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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May 1993
Revised March 1999

74LVX74
Low Voltage Dual D-Type Positive Edge-Triggered Flip-Flop

General Description

The LVX74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

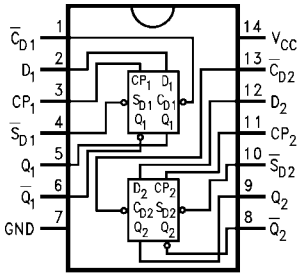
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

Order Number	Package Number	Package Description
74LVX74M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX74MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

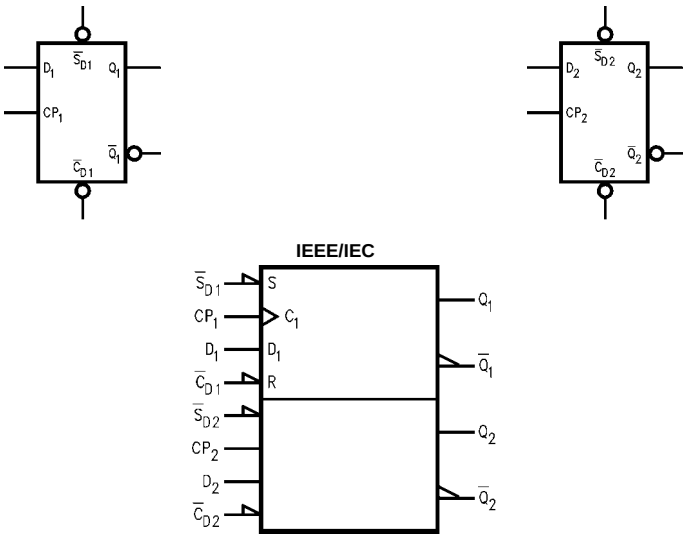
Connection Diagram



Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

Logic Symbols



Truth Table

(Each Half)

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	⌐	H	H	L
H	H	⌐	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
$Q_0(\overline{Q}_0)$ = Previous Q($\overline{Q}$) before LOW-to-HIGH Transition of Clock

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} +0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 µA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 µA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum High Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3 ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	2.7		7.3	15	1.0	18.5	ns	15
t_{PHL}	CP_n to Q_n or $\overline{Q}_n$			9.8	18.5	1.0	22		50
		3.3 ± 0.3		5.7	9.7	1.0	11.5		15
				8.2	13.2	1.0	15		50
t_{PLH}	Propagation Delay	2.7		8.4	15.6	1.0	18.5	ns	15
t_{PHL}	$\overline{C}_{Dn}$ to $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$			10.9	19.1	1.0	22		50
		3.3 ± 0.3		6.6	10.1	1.0	12		15
				9.1	13.6	1.0	15.5		50
t_W	CP_n or $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$	2.7	8.5			10		ns	
	Pulse Width	3.3 ± 0.3	6			7			
t_S	Setup Time	2.7	8.0			9.5		ns	
	D_n to CP_n	3.3 ± 0.3	5.5			6.5			
t_H	Hold Time	2.7	0.5			0.5		ns	
	D_n to CP_n	3.3 ± 0.3	0.5			0.5			
t_{REC}	Recovery Time	2.7	6.5			7.5		ns	
	$\overline{CP}_n$ or $\overline{S}_{Dn}$ to CP_n	3.3 ± 0.3	5.0			5.0			
f_{MAX}	Maximum Clock Frequency	2.7	55	135		50		MHz	15
			45	60		40			50
		3.3 ± 0.3	95	145		80			15
			60	85		50			50
t_{OSLH}	Output to Output Skew	2.7			1.5		1.5	ns	50
t_{OSHL}	(Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSLH} = |t_{PHLm} - t_{PHLn}|$

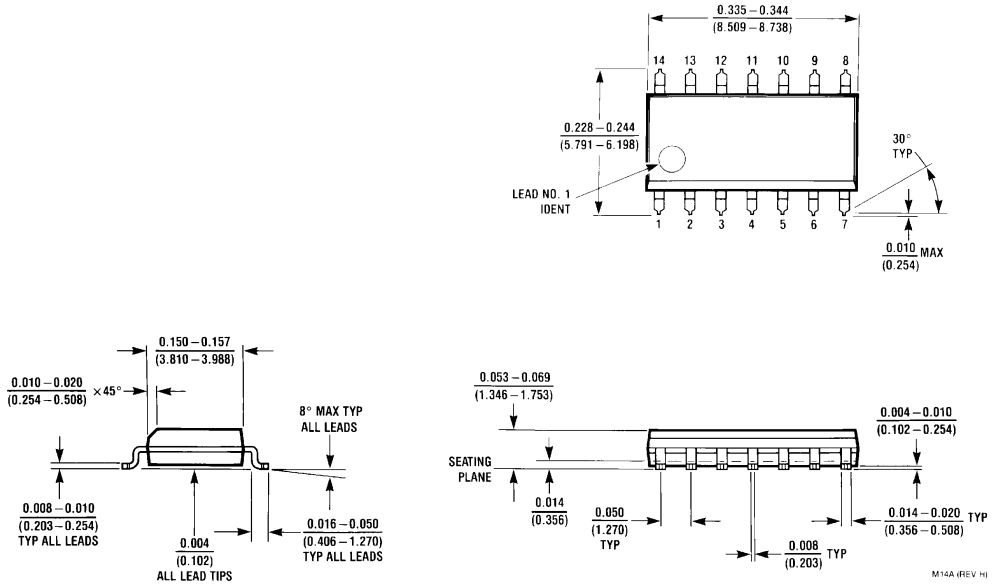
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		25				pF

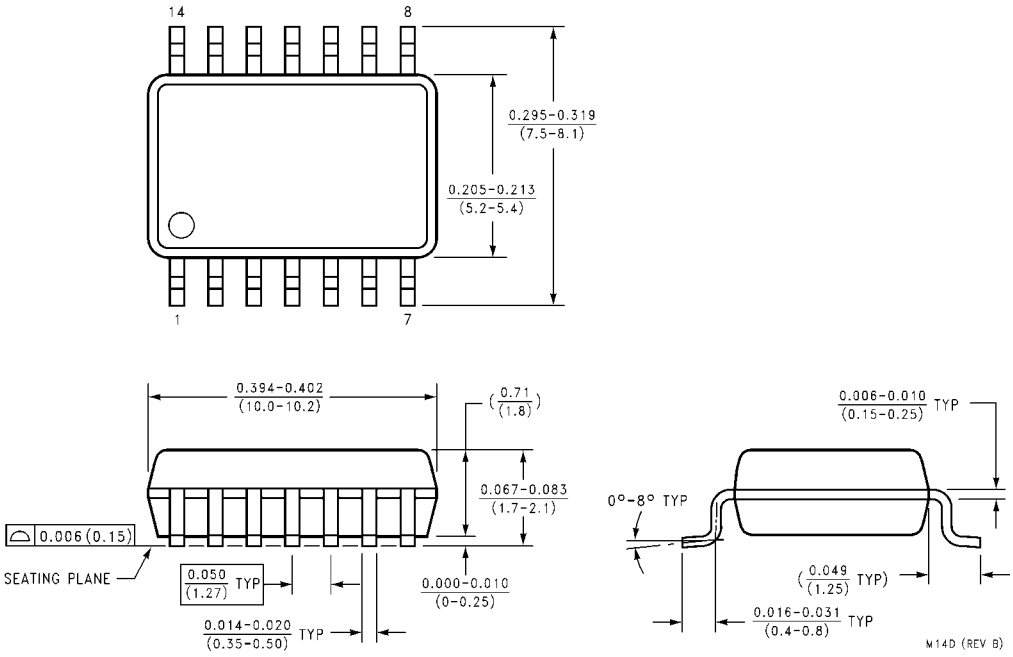
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{2 \text{ (per F/F)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

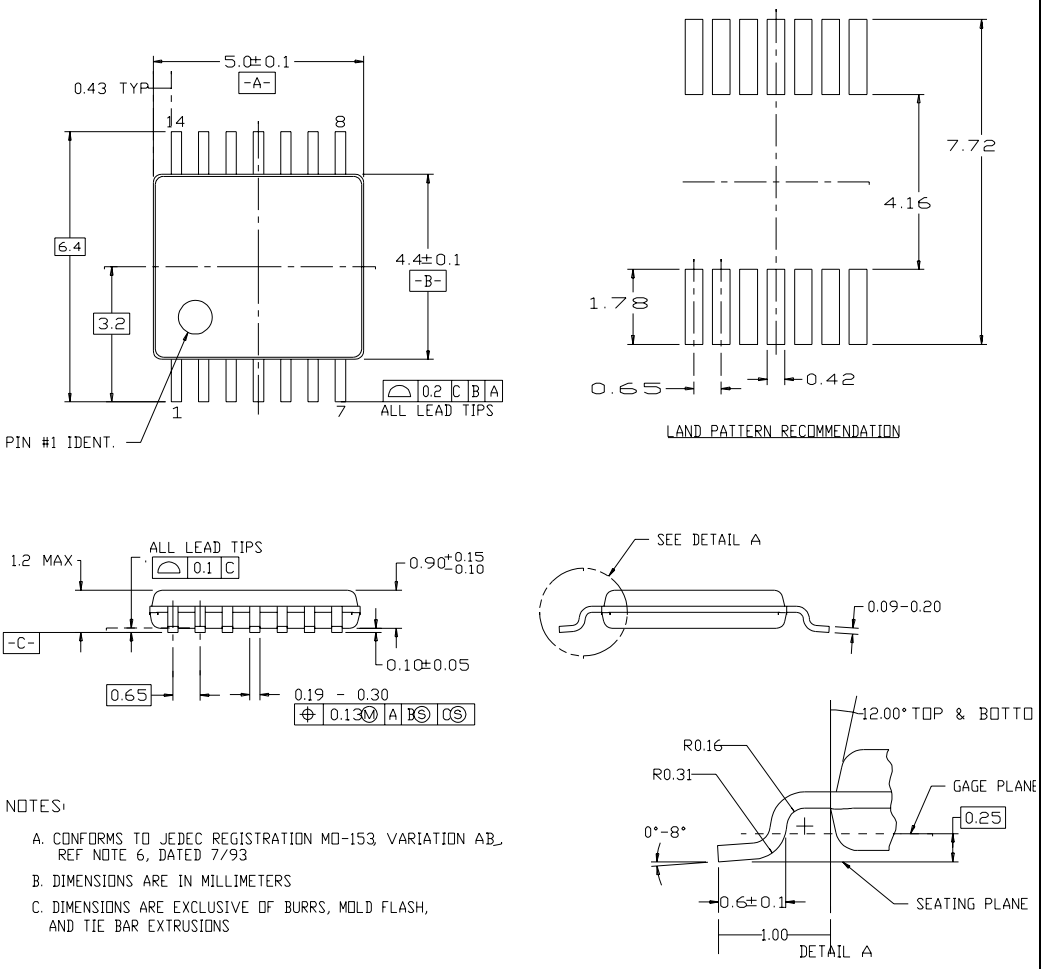


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

May 1993
Revised March 1999

74LVX86
Low Voltage Quad 2-Input Exclusive-OR Gate

General Description

The LVX86 contains four 2-input exclusive-OR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

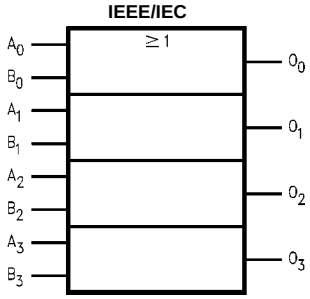
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

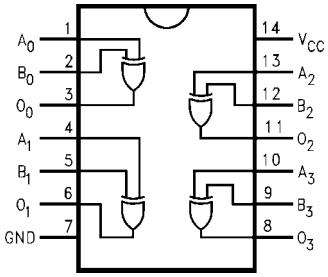
Order Number	Package Number	Package Description
74LVX86M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVX86SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_3	Inputs
B_0–B_3	Inputs
O_0–O_3	Outputs

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time (Δt/ΔV)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA
	Output Voltage	3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.3	−0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input t_r = t_f = 3ns

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	C_L (pF)
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		7.5	14.5	1.0	17.5	ns	15
t_{PHL}	Delay Time			10.0	18.0	1.0	21.0		50
		3.3 ± 0.3		5.8	9.3	1.0	11.0		15
				8.3	12.8	1.0	14.5		50
t_{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t_{OSHL}	Skew (Note 4)	3.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

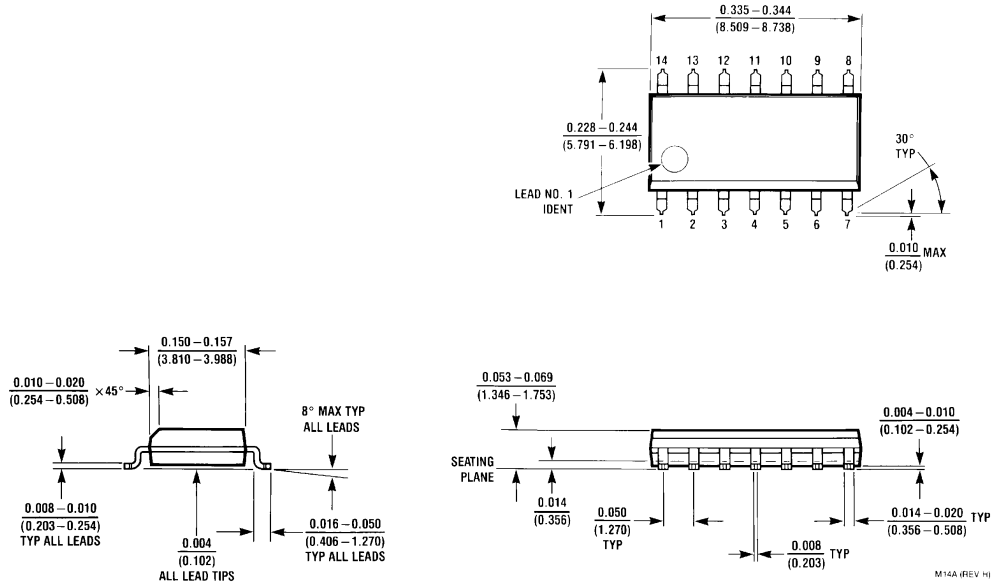
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)		18				pF

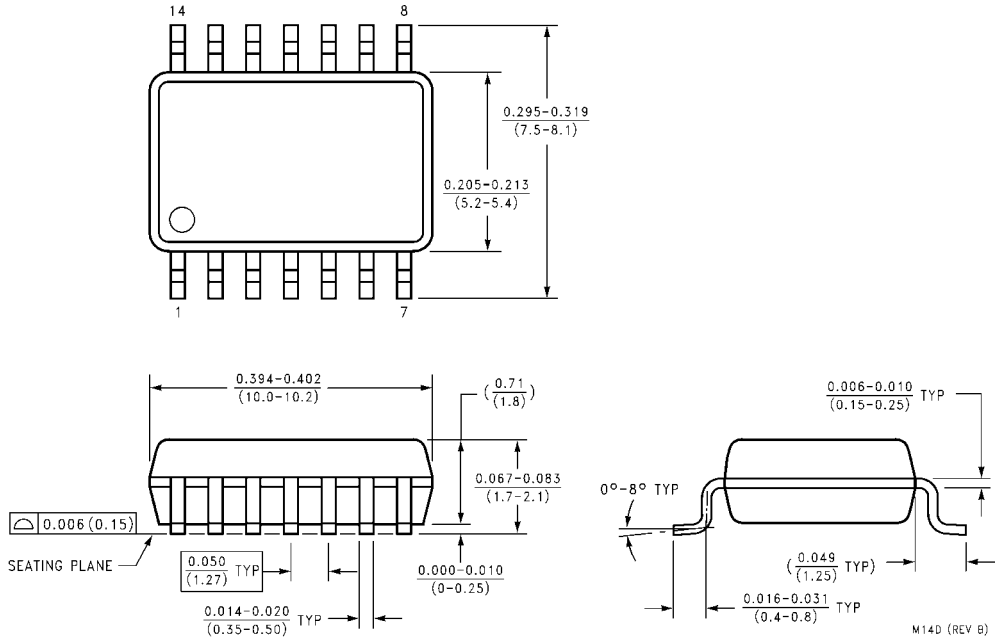
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per Gate)}}$

Physical Dimensions inches (millimeters) unless otherwise noted

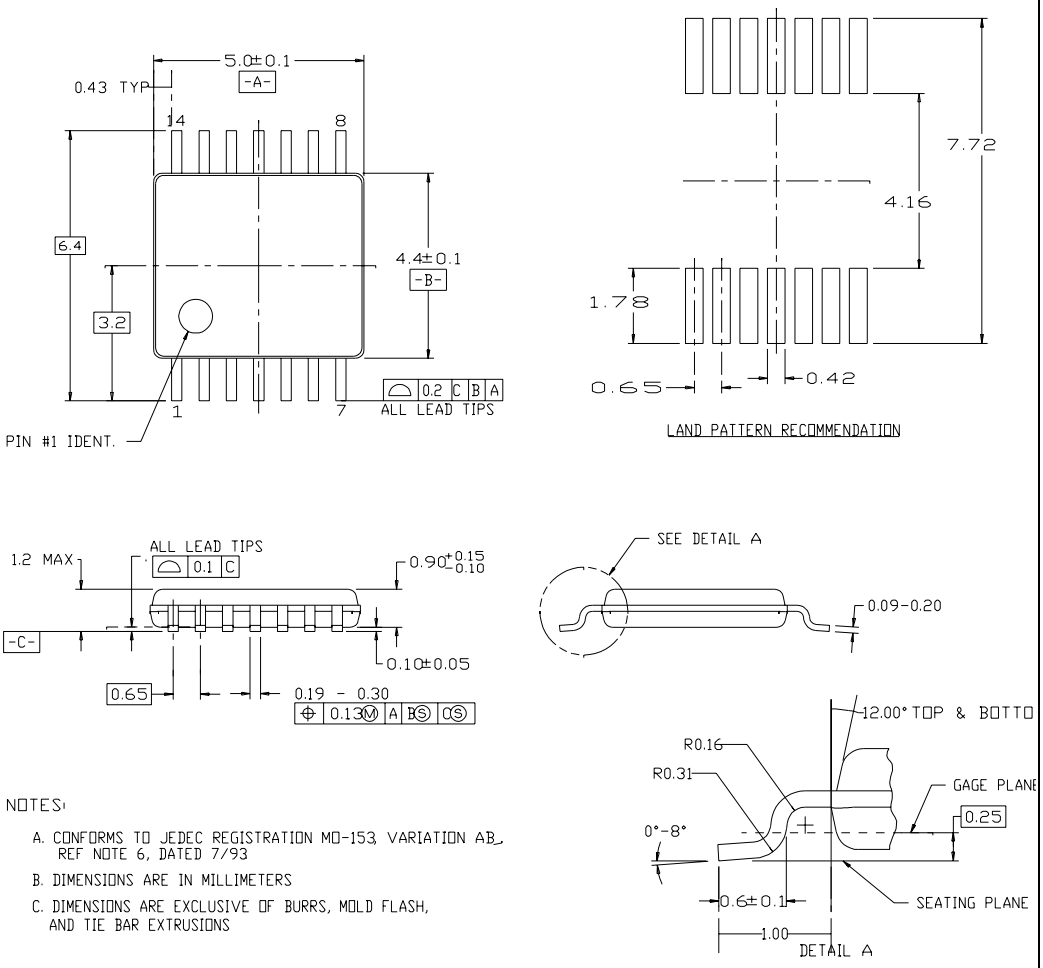


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1994
Revised July 1999

74LVXC3245
8-Bit Dual Supply Configurable Voltage Interface Transceiver with 3-STATE Outputs

General Description

The LVXC3245 is a 24-pin dual-supply, 8-bit configurable voltage interface transceiver suited for PCMCIA and other real time configurable I/O applications. The V_{CCA} pin accepts a 3V supply level. The A Port is a dedicated 3V port. The V_{CCB} pin accepts a 3V-to-5V supply level. The B Port is configured to track the V_{CCB} supply level respectively. A 5V level on the V_{CC} pin will configure the I/O pins at a 5V level and a 3V V_{CC} will configure the I/O pins at a 3V level. The A Port should interface with a 3V host system and the B Port to the card slots. This device will allow the V_{CCB} voltage source pin and I/O pins on the B Port to float when $\overline{OE}$ is HIGH. This feature is necessary to buffer data to and from a PCMCIA socket that permits PCMCIA cards to be inserted and removed during normal operation.

Features

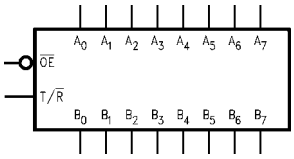
- Bidirectional interface between 3V and 3V-to-5V buses
- Control inputs compatible with TTL level
- Outputs source/sink up to 24 mA
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Implements patented EMI reduction circuitry
- Flexible V_{CCB} operating range
- Allows B Port and V_{CCB} to float simultaneously when $\overline{OE}$ is HIGH
- Functionally compatible with the 74 series 245

Ordering Code:

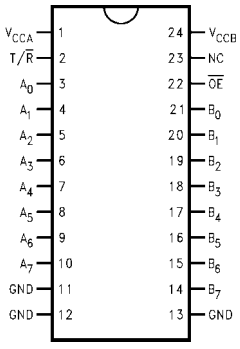
Order Number	Package Number	Package Description
74LVXC3245WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVXC3245QSC	MQA24	24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74LVXC3245MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

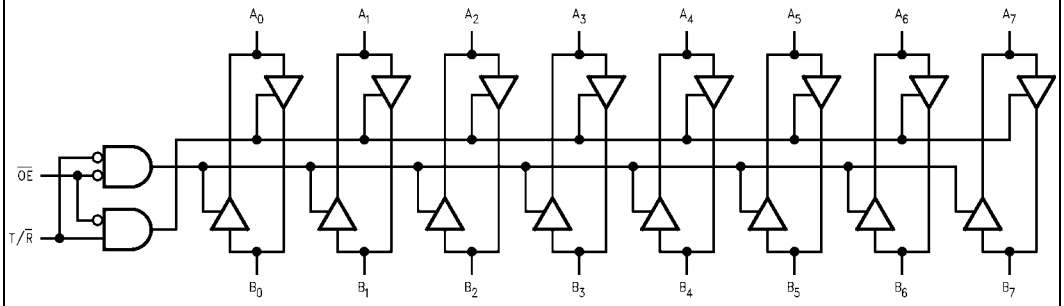
Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CCA}, V_{CCB})	−0.5V to +7.0V
DC Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	−0.5V to V_{CCA} +0.5V
DC Input/Output Voltage ($V_{I/O}$)	
@ A_n	−0.5V to V_{CCA} +0.5V
@ B_n	−0.5V to V_{CCB} +0.5V
DC Input Diode Current (I_{IK})	
@ $\overline{OE}$, T/$\overline{R}$	±20 mA
DC Output Diode (I_{OK}) Current	±50 mA
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
and Max Current	±200 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage	
V_{CCA}	2.7V to 3.6V
V_{CCB}	3.0V to 5.5V
Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	0V to V_{CCA}
Input Output Voltage ($V_{I/O}$)	
@ A_n	0V to V_{CCA}
@ B_n	0V to V_{CCB}
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	8 ns/V
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: The A Port unused pins (inputs or I/Os) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	T_A = 25°C	T_A = −40°C to +85°C		Units	Conditions
					Typ	Guaranteed Limits			
V_{IHA}	Minimum HIGH Level Input Voltage	A_n, $\overline{OE}$ T/$\overline{R}$	2.7	3.0		2.0	2.0	V	$V_{OUT} \le 0.1V$ or $\ge V_{CC} - 0.1V$
			3.0	3.6		2.0	2.0		
			3.6	5.5		2.0	2.0		
V_{IHB}		B_n	2.7	3.0		2.0	2.0		
			3.0	3.6		2.0	2.0		
			3.6	5.5		3.85	3.85		
V_{ILA}	Maximum LOW Level Input Voltage	A_n, $\overline{OE}$ T/$\overline{R}$	2.7	3.0		0.8	0.8	V	$V_{OUT} \le 0.1V$ or $\ge V_{CC} - 0.1V$
			3.0	3.6		0.8	0.8		
			3.6	5.5		0.8	0.8		
V_{ILB}		B_n	2.7	3.0		0.8	0.8		
			3.0	3.6		0.8	0.8		
			3.6	5.5		1.65	1.65		
V_{OHA}	Minimum HIGH Level Output Voltage		3.0	3.0	2.99	2.9	2.9	V	I_{OUT} = −100 μA
			3.0	3.0	2.85	2.56	2.46		I_{OH} = −12 mA
			3.0	3.0	2.65	2.35	2.25		I_{OH} = −24 mA
			2.7	3.0	2.5	2.3	2.2		I_{OH} = −12 mA
			2.7	4.5	2.3	2.1	2.0		I_{OH} = −24 mA
V_{OHB}			3.0	3.0	2.99	2.9	2.9	V	I_{OUT} = −100 μA
			3.0	3.0	2.85	2.56	2.46		I_{OH} = −12 mA
			3.0	3.0	2.65	2.35	2.25		I_{OH} = −24 mA
			3.0	4.5	4.25	3.86	3.76		I_{OH} = −24 mA
V_{OLA}	Maximum LOW Level Output Voltage		3.0	3.0	0.002	0.1	0.1	V	I_{OUT} = 100 μA
			3.0	3.0	0.21	0.36	0.44		I_{OL} = 24 mA
			2.7	3.0	0.11	0.36	0.44		I_{OL} = 12 mA
			2.7	4.5	0.22	0.42	0.5		I_{OL} = 24 mA
V_{OLB}			3.0	3.0	0.002	0.1	0.1	V	I_{OUT} = 100 μA
			3.0	3.0	0.21	0.36	0.44		I_{OL} = 24 mA
			3.0	4.5	0.18	0.36	0.44		I_{OL} = 24 mA
I_{IN}	Maximum Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		3.6	3.6		±0.1	±1.0	μA	$V_I = V_{CCA}$, GND
			3.6	5.5		±0.1	±1.0		

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
					Typ	Guaranteed Limits			
I_{OZA}	Maximum 3-STATE Output Leakage @ A_n		3.6 3.6	3.6 5.5		±0.5 ±0.5	±5.0 ±5.0	µA	$V_I = V_{IL}$, V_{IH}, $\overline{OE} = V_{CCA}$ $V_O = V_{CCA}$, GND
I_{OZB}	Maximum 3-STATE Output Leakage @ B_n		3.6 3.6	3.6 5.5		±0.5 ±0.5	±5.0 ±5.0	µA	$V_I = V_{IL}$, V_{IH}, $\overline{OE} = V_{CCA}$ $V_O = V_{CCB}$, GND
ΔI_{CC}	Maximum I_{CC}/Input	B_n	3.6	5.5	1.0	1.35	1.5	mA	$V_I = V_{CCB}-2.1V$
		All Inputs	3.6	3.6		0.35	0.5		$V_I = V_{CC}-0.6V$
I_{CCA1}	Quiescent V_{CCA} Supply Current as B Port Floats		3.6	Open		5	50	µA	$A_n = V_{CCA}$ or GND B_n = Open, $\overline{OE} = V_{CCA}$, $T/\overline{R} = V_{CCA}$, V_{CCB} = Open
I_{CCA2}	Quiescent V_{CCA} Supply Current		3.6 3.6	3.6 5.5		5 5	50 50	µA	$A_n = V_{CCA}$ or GND, $B_n = V_{CCB}$ or GND, $\overline{OE}$ = GND, $T/\overline{R}$ = GND
I_{CCB}	Quiescent V_{CCB} Supply Current		3.6 3.6	3.6 5.5		5 8	50 80	µA	$A_n = V_{CCA}$ or GND, $B_n = V_{CCB}$ or GND, $\overline{OE}$ = GND, $T/\overline{R} = V_{CCA}$
V_{OLPA}	Quiet Output Maximum Dynamic		3.3 3.3	3.3 5.0		0.8 0.8		V	(Note 3)(Note 4)
V_{OLPB}	V_{OL}		3.3 3.3	3.3 5.0		0.8 1.5		V	(Note 3)(Note 4)
V_{OLVA}	Quiet Output Minimum Dynamic		3.3 3.3	3.3 5.0		–0.8 –0.8		V	(Note 3)(Note 4)
V_{OLVB}	V_{OL}		3.3 3.3	3.3 5.0		–0.8 –1.2		V	(Note 3)(Note 4)
V_{IHDA}	Minimum HIGH Level Dynamic		3.3 3.3	3.3 5.0		2.0 2.0		V	(Note 3)(Note 5)
V_{IHDB}	Input Voltage		3.3 3.3	3.3 5.0		2.0 3.5		V	(Note 3)(Note 5)
V_{ILDA}	Maximum LOW Level Dynamic		3.3 3.3	3.3 5.0		0.8 0.8		V	(Note 3)(Note 5)
V_{ILDB}	Input Voltage		3.3 3.3	3.3 5.0		0.8 1.5		V	(Note 3)(Note 5)

Note 3: Worst case package.

Note 4: Max number of outputs defined as (n). Data inputs are driven 0V to V_{CC} level; one output at GND.

Note 5: Max number of Data Inputs (n) switching. (n–1) inputs switching 0V to V_{CC} level. Input-under-test switching: V_{CC} level to threshold (V_{IHD}), 0V to threshold (V_{ILD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $C_L = 50$ pF, $V_{CCA} = 2.7V–3.6V$, $V_{CCB} = 4.5V–5.5V$			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $V_{CCA} = 2.7V–3.6V$, $V_{CCB} = 4.5V–5.5V$		$T_A = +25°C$, $C_L = 50$ pF, $V_{CCA} = 2.7V–3.6V$, $V_{CCB} = 3.0V–3.6V$			$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF, $V_{CCA} = 2.7V–3.6V$, $V_{CCB} = 3.0V–3.6V$		Units
		Min	Typ (Note 6)	Max	Min	Max	Min	Typ (Note 7)	Max	Min	Max	
t_{PHL}	Propagation Delay	1.0	4.8	8.0	1.0	8.5	1.0	5.5	8.5	1.0	9.0	ns
t_{PLH}	A to B	1.0	3.9	6.5	1.0	7.0	1.0	5.2	8.0	1.0	8.5	
t_{PHL}	Propagation Delay	1.0	3.8	6.5	1.0	7.0	1.0	4.4	7.0	1.0	7.5	ns
t_{PLH}	B to A	1.0	4.3	7.5	1.0	8.0	1.0	5.1	7.5	1.0	8.0	
t_{PZL}	Output Enable Time	1.0	4.7	8.0	1.0	8.5	1.0	6.0	9.0	1.0	9.5	ns
t_{PZH}	$\overline{OE}$ to B	1.0	4.8	8.5	1.0	9.0	1.0	6.1	9.5	1.0	10.0	
t_{PZL}	Output Enable Time	1.0	5.9	9.5	1.0	10.0	1.0	6.4	10.0	1.0	10.5	ns
t_{PZH}	$\overline{OE}$ to A	1.0	5.4	9.0	1.0	9.5	1.0	5.8	9.0	1.0	9.5	
t_{PHZ}	Output Disable Time	1.0	4.0	8.0	1.0	8.5	1.0	6.3	9.5	1.0	10.0	ns
t_{PLZ}	$\overline{OE}$ to B	1.0	3.8	7.5	1.0	8.0	1.0	4.5	8.0	1.0	8.5	
t_{PHZ}	Output Disable Time	1.0	4.6	9.5	1.0	10.0	1.0	5.2	9.5	1.0	10.0	ns
t_{PLZ}	$\overline{OE}$ to A	1.0	3.1	6.5	1.0	7.0	1.0	3.4	6.5	1.0	7.0	
t_{OSHL}	Output to Output											
t_{OSLH}	Skew (Note 8)		1.0	1.5		1.5		1.0	1.5		1.5	ns
	Data to Output											

Note 6: Typical values at $V_{CCA} = 3.3V$, $V_{CCB} = 5.0V$ @ 25°C.

Note 7: Typical values at $V_{CCA} = 3.3V$, $V_{CCB} = 3.3V$ @ 25°C.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter		Typ	Units	Conditions
C_{IN}	Input Capacitance		4.5	pF	V_{CC} = Open
$C_{I/O}$	Input/Output Capacitance		10	pF	$V_{CCA} = 3.3V$ $V_{CCB} = 5.0V$
C_{PD}	Power Dissipation	A→B	50	pF	$V_{CCB} = 5.0V$
	Capacitance (Note 9)	B→A	40	pF	$V_{CCA} = 3.3V$

Note 9: C_{PD} is measured at 10 MHz.

Power Up Considerations

To insure the system does not experience unnecessary I_{CC} current draw, bus contention, or oscillations during power up, the following guidelines should be adhered to (refer to Table 1):

- Power up the control side of the device first. This is the V_{CCA} side.
- $\overline{OE}$ should ramp with or ahead of V_{CCA}. This will help guard against bus contention.
- The Transmit/Receive control pin (T/$\overline{R}$) should ramp with V_{CCA}, this will ensure that the A Port data pins are configured as inputs. With V_{CCA} receiving power first, the A I/O Port should be configured as inputs to help guard against bus contention and oscillations.
- A side data inputs should be driven to a valid logic level. This will prevent excessive current draw.

The above steps will ensure that no bus contention or oscillations, and therefore no excessive current draw occurs during the power up cycling of these devices. These steps will help prevent possible damage to the translator devices and potential damage to other system components.

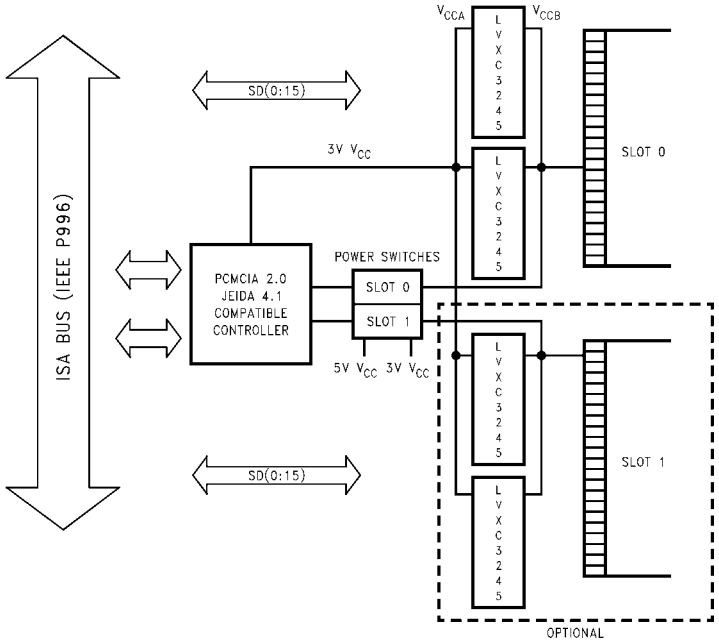
TABLE 1. Low Voltage Translator Power Up Sequencing Table

Device Type	V_{CCA}	V_{CCB}	T/$\overline{R}$	$\overline{OE}$	A Side I/O	B Side I/O	Floatable Pin Allowed
74LVXC3245	3V (power up 1st)	3V to 5.5V configurable	ramp with V_{CCA}	ramp with V_{CCA}	logic 0V or V_{CCA}	outputs	yes, V_{CCB} and B I/O's w/ $\overline{OE}$ HIGH

Please reference Application Note AN-5001 for more detailed information on using Fairchild's LVX Low Voltage Dual Supply CMOS Translating Transceivers.

Configurable I/O Application for PCMCIA Cards

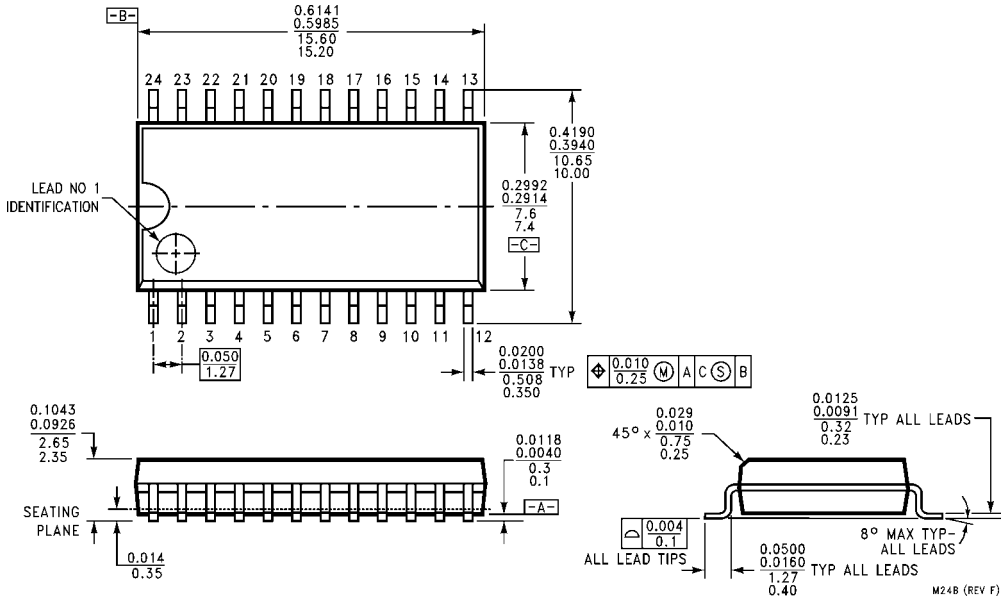
Block Diagram



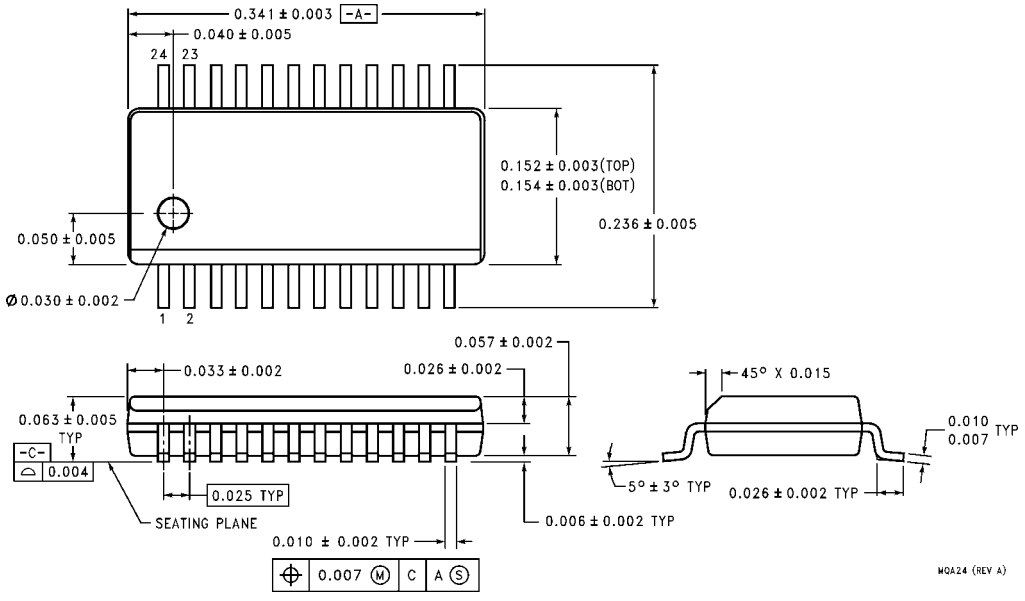
The LVXC3245 is a 24-pin dual supply device well suited for PCMCIA configurable I/O applications. Ideal for low power notebook designs, the LVXC3245 consumes less than 1 mW of quiescent power in all modes of operation. The LVXC3245 meets all PCMCIA I/O voltage requirements at 5V and 3.3V operation. By tying V_{CCB} of the LVXC3245 to the card voltage supply, the PCMCIA card will always experience rail to rail output swings, maximizing the reliability of the interface.

The V_{CCA} pin on the LVXC3245 must always be tied to a 3V power supply. This voltage connection provides internal references needed to account for variations in V_{CCB}. When connected as in the figure above, the LVXC3245 meets all the voltage and current requirements of the ISA bus standard (IEEE P996).

Physical Dimensions inches (millimeters) unless otherwise noted

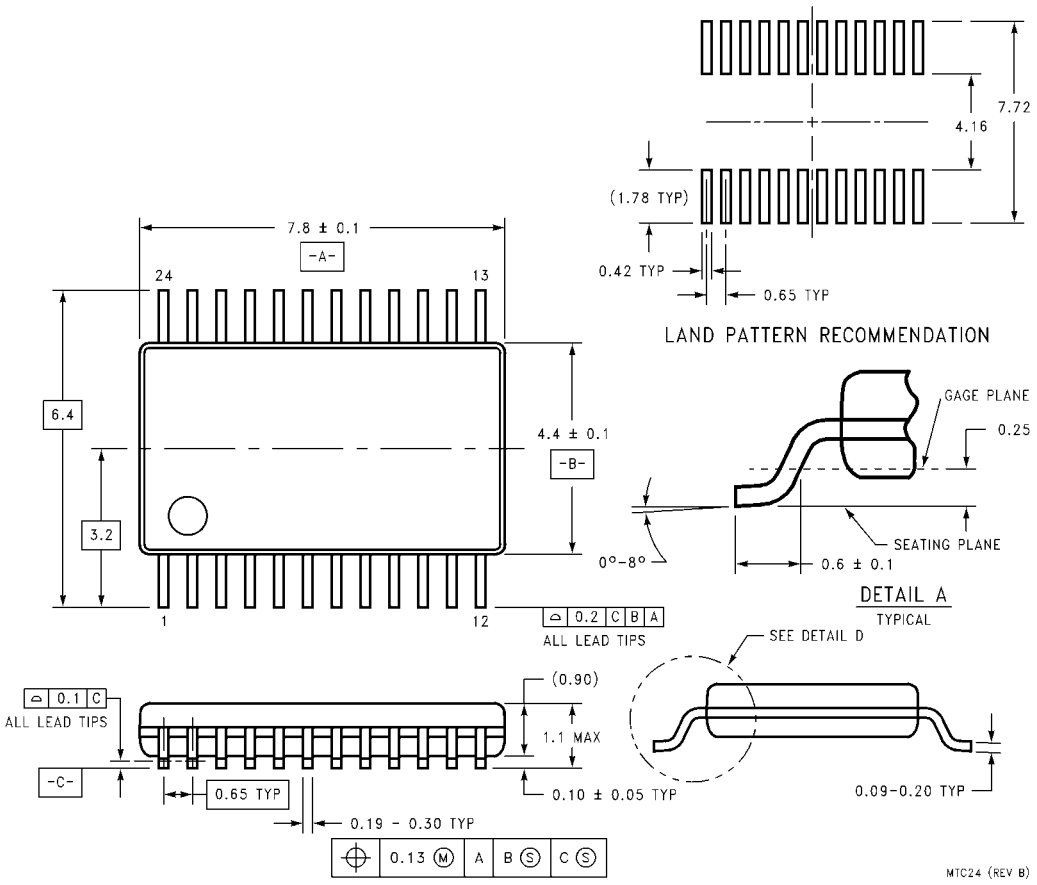


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-37, 0.150" Wide
Package Number MQA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

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February 1994
Revised July 1999

74LVXC4245
8-Bit Dual Supply Configurable Voltage Interface Transceiver with 3-STATE Outputs

General Description

The LVXC4245 is a 24-pin dual-supply, 8-bit configurable voltage interface transceiver suited for PCMCIA and other real time configurable I/O applications. The V_{CCA} pin accepts a 5V supply level. The "A" Port is a dedicated 5V port. The V_{CCB} pin accepts a 3V-to-5V supply level. The "B" Port is configured to track the V_{CCB} supply level respectively. A 5V level on the V_{CC} pin will configure the I/O pins at a 5V level and a 3V V_{CC} will configure the I/O pins at a 3V level. This device will allow the V_{CCB} voltage source pin and I/O pins on the "B" Port to float when $\overline{OE}$ is HIGH. This feature is necessary to buffer data to and from a PCMCIA socket that permits PCMCIA cards to be inserted and removed during normal operation.

Features

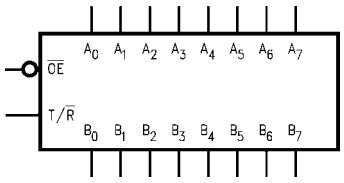
- Bidirectional interface between 5V and 3V-to-5V buses
- Control inputs compatible with TTL level
- Outputs source/sink up to 24 mA
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Implements patented EMI reduction circuitry
- Flexible V_{CCB} operating range
- Allows B Port and V_{CCB} to float simultaneously when $\overline{OE}$ is HIGH
- Functionally compatible with the 74 series 245

Ordering Code:

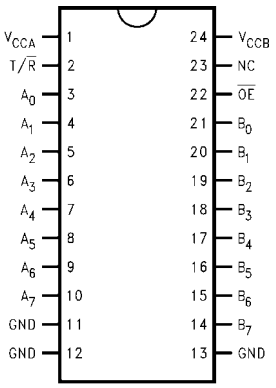
Order Number	Package Number	Package Description
74LVXC4245WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVXC4245QSC	MQA24	24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
74LVXC4245MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

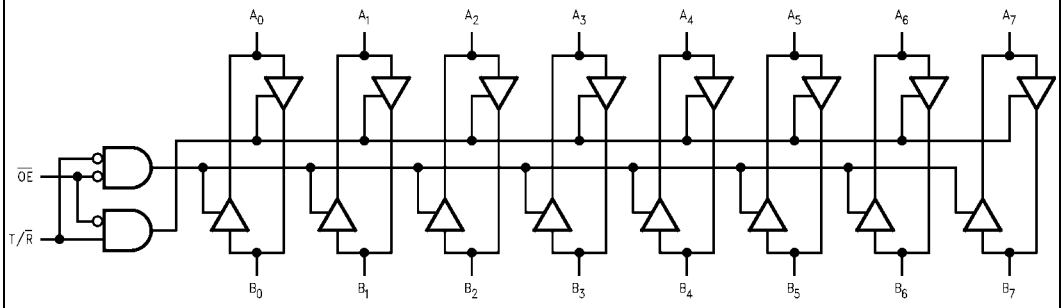
Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CCA},V_{CCB})	−0.5V to +7.0V
DC Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	−0.5V to V_{CCA} +0.5V
DC Input/Output Voltage ($V_{I/O}$)	
@ A_n	−0.5V to V_{CCA} +0.5V
@ B_n	−0.5V to V_{CCB} +0.5V
DC Input Diode Current (I_{IK})	
@ $\overline{OE}$, T/$\overline{R}$	±20 mA
DC Output Diode Current (I_{OK})	±50 mA
DC Output Source or	
Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
Per Output Pin (I_{CC} or I_{GND})	±50 mA
and Max Current	±200 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
DC Latch-Up Source or	
Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage V_{CCA}	4.5V to 5.5V
V_{CCB}	2.7V to 5.5V
Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	0V to V_{CCA}
Input/Output Voltage ($V_{I/O}$)	
@A_n	0V to V_{CCA}
@B_n	0V to V_{CCB}
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	8 ns/V
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3V, 4.5V, 5.5V	

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: The A Port unused pins (inputs and I/O's) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
					Typ	Guaranteed Limits			
V_{IHA}	Minimum HIGH Level	A_n	4.5	2.7		2.0	2.0	V	$V_{OUT} \le 0.1V$
	Input Voltage	$\overline{OE}$	4.5	3.6		2.0	2.0		or
		T/$\overline{R}$	5.5	5.5		2.0	2.0		$\ge V_{CC} - 0.1V$
V_{IHB}		B_n	4.5	2.7		2.0	2.0		
			4.5	3.6		2.0	2.0		
			4.5	5.5		3.85	3.85		
V_{ILA}	Maximum LOW Level	A_n	4.5	2.7		0.8	0.8	V	$V_{OUT} \le 0.1V$
	Input Voltage	$\overline{OE}$	4.5	3.6		0.8	0.8		or
		T/$\overline{R}$	5.5	5.5		0.8	0.8		$\ge V_{CC} - 0.1V$
V_{ILB}		B_n	4.5	2.7		0.8	0.8		
			4.5	3.6		0.8	0.8		
			4.5	5.5		1.65	1.65		
V_{OHA}	Minimum HIGH Level		4.5	3.0	4.49	4.4	4.4	V	$I_{OUT} = -100\ \mu A$
	Output Voltage		4.5	3.0	4.25	3.86	3.76		$I_{OH} = -24$ mA
V_{OHB}			4.5	3.0	2.99	2.9	2.9	V	$I_{OUT} = -100\ \mu A$
			4.5	3.0	2.85	2.56	2.46		$I_{OH} = -12$ mA
			4.5	3.0	2.65	2.35	2.25		$I_{OH} = -24$ mA
			4.5	2.7	2.5	2.3	2.2		$I_{OH} = -12$ mA
			4.5	2.7	2.3	2.1	2.0		$I_{OH} = -24$ mA
			4.5	4.5	4.25	3.86	3.76		$I_{OH} = -24$ mA
V_{OLA}	Maximum LOW Level		4.5	3.0	0.002	0.1	0.1	V	$I_{OUT} = 100\ \mu A$
	Output Voltage		4.5	3.0	0.21	0.36	0.44		$I_{OL} = 24$ mA
V_{OLB}			4.5	3.0	0.002	0.1	0.1	V	$I_{OUT} = 100\ \mu A$
			4.5	3.0	0.21	0.36	0.44		$I_{OL} = 24$ mA
			4.5	2.7	0.11	0.36	0.44		$I_{OL} = 12$ mA
			4.5	2.7	0.22	0.42	0.5		$I_{OL} = 24$ mA
			4.5	4.5	0.18	0.36	0.44		$I_{OL} = 24$ mA
I_{IN}	Maximum Input							μA	$V_I = V_{CCA}$, GND
	Leakage Current @		5.5	3.6		±0.1	±1.0		
	$\overline{OE}$, T/$\overline{R}$		5.5	5.5		±0.1	±1.0		

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	$T_A = +25°C$	$T_A = -40°C$ to $+85°C$		Units	Conditions
					Typ	Guaranteed Limits			
I_{OZA}	Maximum 3-STATE		5.5	3.6		±0.5	±5.0	μA	$V_I = V_{IL}$, V_{IH}, $\overline{OE} = V_{CCA}$
	Output Leakage @ A_n		5.5	5.5		±0.5	±5.0		$V_O = V_{CCA}$, GND
I_{OZB}	Maximum 3-STATE		5.5	3.6		±0.5	±5.0	μA	$V_I = V_{IL}$, V_{IH}, $\overline{OE} = V_{CCA}$
	Output Leakage @ B_n		5.5	5.5		±0.5	±5.0		$V_O = V_{CCB}$, GND
ΔI_{CC}	Maximum	All Inputs	5.5	5.5	1.0	1.35	1.5	mA	$V_I = V_{CC} - 2.1V$
	I_{CC}/Input	B_n	5.5	3.6		0.35	0.5	mA	$V_I = V_{CCB} - 0.6V$
I_{CCA1}	Quiescent V_{CCA} Supply Current as B Port Floats		5.5	Open		8	80	μA	$A_n = V_{CCA}$ or GND B_n = Open, $\overline{OE} = V_{CCA}$ $T/\overline{R} = V_{CCA}$, V_{CCB} = Open
I_{CCA2}	Quiescent V_{CCA} Supply Current							μA	$A_n = V_{CCA}$ or GND $B_n = V_{CCB}$ or GND $\overline{OE}$ = GND, $T/\overline{R}$ = GND
			5.5	3.6		8	80		
			5.5	5.5		8	80		
I_{CCB}	Quiescent V_{CCB} Supply Current							μA	$A_n = V_{CCA}$ or GND $B_n = V_{CCB}$ or GND $\overline{OE}$ = GND, $T/\overline{R} = V_{CCA}$
			5.5	3.6		5	50		
			5.5	5.5		8	80		
V_{OLPA}	Quiet Output		5.0	3.3		1.5		V	(Note 3) (Note 4)
	Maximum Dynamic		5.0	5.0		1.5			
V_{OLPB}	V_{OL}		5.0	3.3		0.8		V	(Note 3) (Note 4)
			5.0	5.0		1.5			
V_{OLVA}	Quiet Output Minimum		5.0	3.3		−1.2		V	(Note 3) (Note 4)
	Dynamic V_{OL}		5.0	5.0		−1.2			
V_{OLVB}			5.0	3.3		−0.8		V	(Note 3) (Note 4)
			5.0	5.0		−1.2			
V_{IHDA}	Minimum HIGH Level		5.0	3.3		2.0		V	(Note 3) (Note 5)
	Dynamic Input		5.0	5.0		2.0			
V_{IHDB}	Voltage		5.0	3.3		2.0		V	(Note 3) (Note 5)
			5.0	5.0		3.5			
V_{ILDA}	Maximum LOW Level		5.0	3.3		0.8		V	(Note 3) (Note 5)
	Dynamic Input		5.0	5.0		0.8			
V_{ILDB}	Voltage		5.0	3.3		0.8		V	(Note 3) (Note 5)
			5.0	5.0		1.5			

Note 3: Worst case package.

Note 4: Max number of outputs defined as (n). Data inputs are driven 0V to V_{CC} level; one output at GND.

Note 5: Max number of Data Inputs (n) switching. (n–1) inputs switching 0V to V_{CC} level. Input-under-test switching: V_{CC} level to threshold (V_{IHD}), 0V to threshold (V_{ILD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	C_L = 50 pF, V_{CCA} = 4.5V to 5.5V, V_{CCB} = 4.5V to 5.5V					C_L = 50 pF, V_{CCA} = 4.5V to 5.5V, V_{CCB} = 2.7V to 3.6V					Units
		T_A = +25°C			T_A = −40°C to +85°C		T_A = +25°C			T_A = −40°C to +85°C		
		Min	Typ (Note 6)	Max	Min	Max	Min	Typ (Note 7)	Max	Min	Max	
t_{PHL}	Propagation	1.0	4.9	6.5	1.0	7.0	1.0	5.5	7.5	1.0	8.0	ns
t_{PLH}	Delay A to B	1.0	4.0	5.5	1.0	6.0	1.0	5.0	7.0	1.0	7.5	
t_{PHL}	Propagation	1.0	4.7	6.5	1.0	7.0	1.0	5.6	7.5	1.0	8.0	ns
t_{PLH}	Delay B to A	1.0	3.9	5.0	1.0	5.5	1.0	4.3	6.0	1.0	6.5	
t_{PZL}	Output Enable	1.0	5.6	7.5	1.0	8.0	1.0	6.7	9.0	1.0	10.0	ns
t_{PZH}	Time $\overline{OE}$ to B	1.0	5.7	7.5	1.0	8.0	1.0	6.9	9.5	1.0	10.0	
t_{PZL}	Output Enable	1.0	7.4	9.0	1.0	10.0	1.0	8.0	10.0	1.0	11.0	ns
t_{PZH}	Time $\overline{OE}$ to A	1.0	6.1	7.5	1.0	8.5	1.0	6.3	8.0	1.0	8.5	
t_{PHZ}	Output Disable	1.0	4.8	7.0	1.0	7.5	1.0	6.0	9.0	1.0	9.5	ns
t_{PLZ}	Time $\overline{OE}$ to B	1.0	3.8	5.5	1.0	6.0	1.0	4.2	6.5	1.0	7.0	
t_{PHZ}	Output Disable	1.0	3.4	5.5	1.0	6.0	1.0	3.4	5.5	1.0	6.0	ns
t_{PLZ}	Time $\overline{OE}$ to A	1.0	2.9	4.5	1.0	5.0	1.0	2.9	5.0	1.0	5.5	
t_{OSHL}	Output to Output											ns
t_{OSLH}	Skew (Note 8)		1.0	1.5		1.5		1.0	1.5		1.5	
	Data to Output											

Note 6: Typical values at V_{CCA} = 5V, V_{CCB} = 5V @25°C.

Note 7: Typical values at V_{CCA} = 5V, V_{CCB} = 3.3V @25°C.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter		Typ	Units	Conditions
C_{IN}	Input Capacitance		4.5	pF	V_{CC} = Open
$C_{I/O}$	Input/Output Capacitance		10	pF	V_{CCA} = 5V, V_{CCB} = 3.3V
C_{PD}	Power Dissipation Capacitance	A→B	45	pF	V_{CCA} = 5V
	(Note 9)	B→A	50	pF	V_{CCB} = 3.3V

Note 9: C_{PD} is measured at 10 MHz.

Power Up Considerations

To insure the system does not experience unnecessary I_{CC} current draw, bus contention, or oscillations during power up, the following guidelines should be adhered to (refer to Table 1):

- Power up the control side of the device first. This is the V_{CCA}.
- $\overline{OE}$ should ramp with or ahead of V_{CCA}. This will help guard against bus contention.
- The Transmit/Receive control pin (T/$\overline{R}$) should ramp with V_{CCA}, this will ensure that the A Port data pins are configured as inputs. With V_{CCA} receiving power first, the A I/O Port should be configured as inputs to help guard against bus contention and oscillations.
- A side data inputs should be driven to a valid logic level. This will prevent excessive current draw.

The above steps will ensure that no bus contention or oscillations, and therefore no excessive current draw occurs during the power up cycling of these devices. These steps will help prevent possible damage to the translator devices and potential damage to other system components.

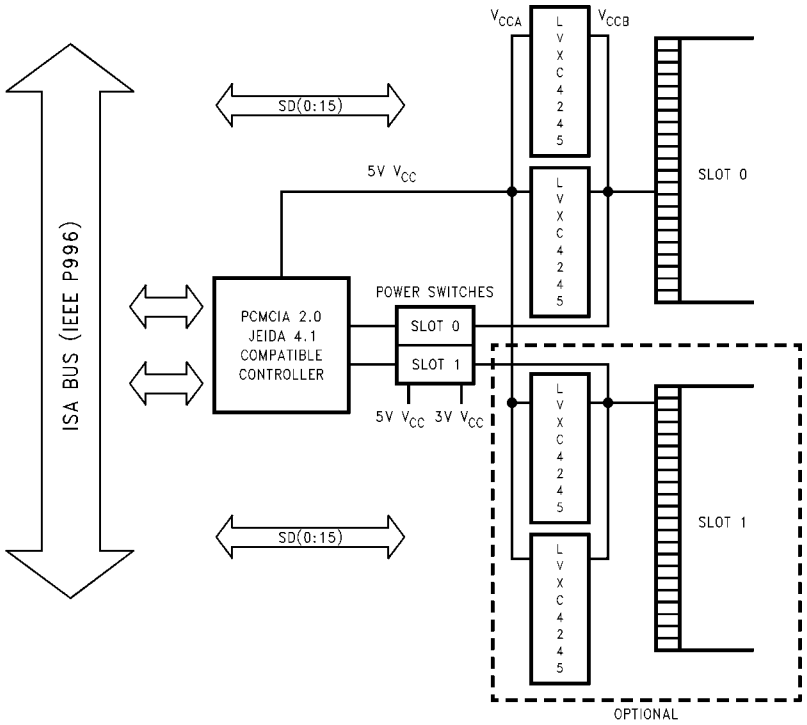
TABLE 1. Low Voltage Translator Power Up Sequencing Table

Device Type	V_{CCA}	V_{CCB}	T/$\overline{R}$	$\overline{OE}$	A Side I/O	B Side I/O	Floatable Pin Allowed
74LVXC4245	5V (power up 1st)	2.7V to 5.5V configurable	ramp with V_{CCA}	ramp with V_{CCA}	logic 0V or V_{CCA}	outputs	yes, V_{CCB} and B I/O's w/ $\overline{OE}$ HIGH

Please reference Application Note AN-5001 for more detailed information on using Fairchild's LVX Low Voltage Dual Supply CMOS Translating Transceivers.

Configurable I/O Application for PCMCIA Cards

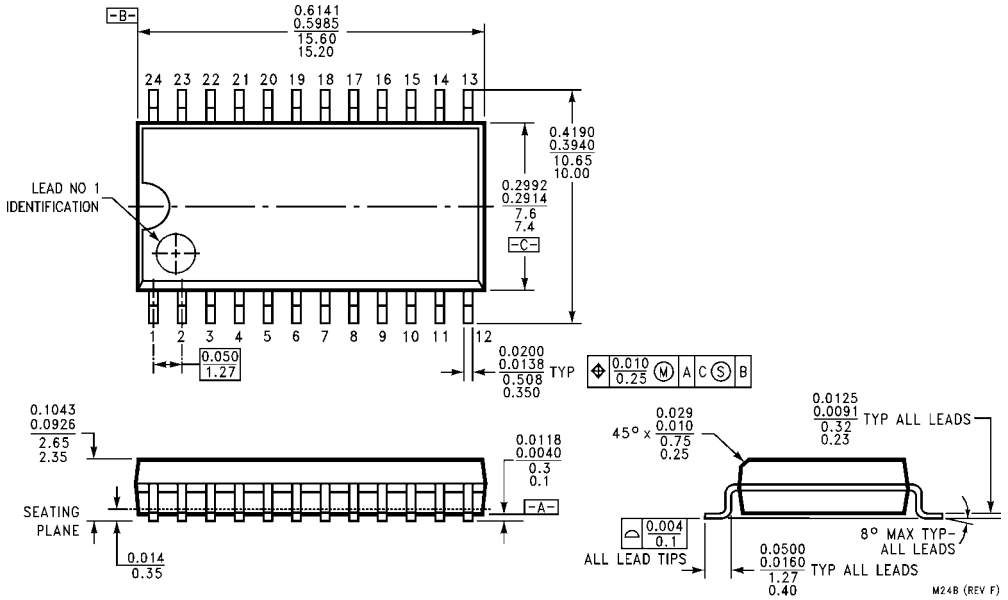
Block Diagram



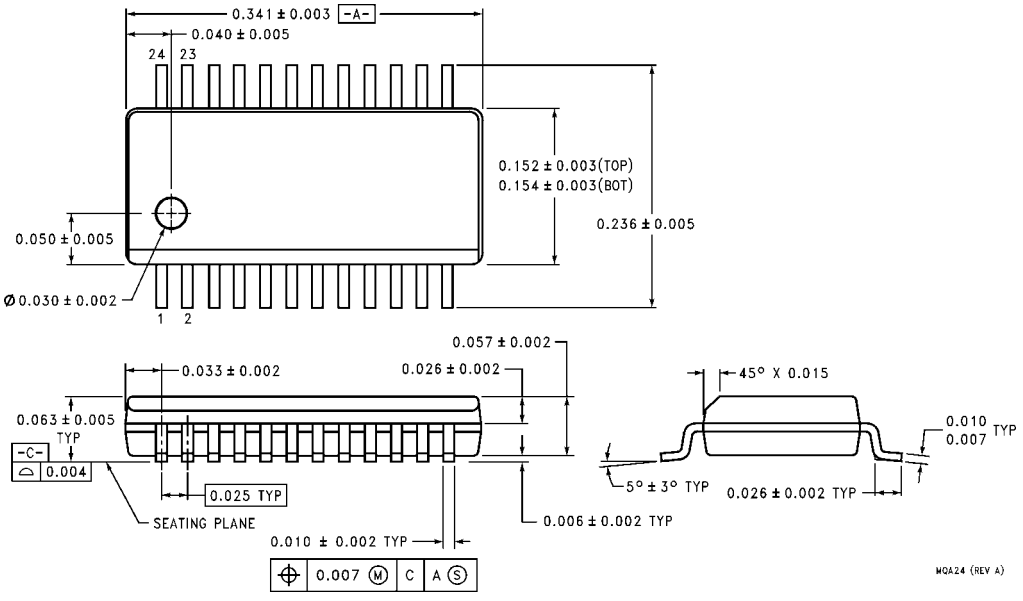
The LVXC4245 is a 24-pin dual supply device well suited for PCMCIA configurable I/O applications. Ideal for low power notebook designs, the LVXC4245 consumes less than 1 mW of quiescent power in all modes of operation. The LVXC4245 meets all PCMCIA I/O voltage requirements at 5V and 3.3V operation. By tying V_{CCB} of the LVXC4245 to the card voltage supply, the PCMCIA card will always experience rail to rail output swings, maximizing the reliability of the interface.

The V_{CCA} pin on the LVXC4245 must always be tied to a 5V power supply. This voltage connection provides internal references needed to account for variations in V_{CCB}. When connected as in the block diagram above, the LVXC4245 meets all the voltage and current requirements of the ISA bus standard (IEEE P996).

Physical Dimensions inches (millimeters) unless otherwise noted

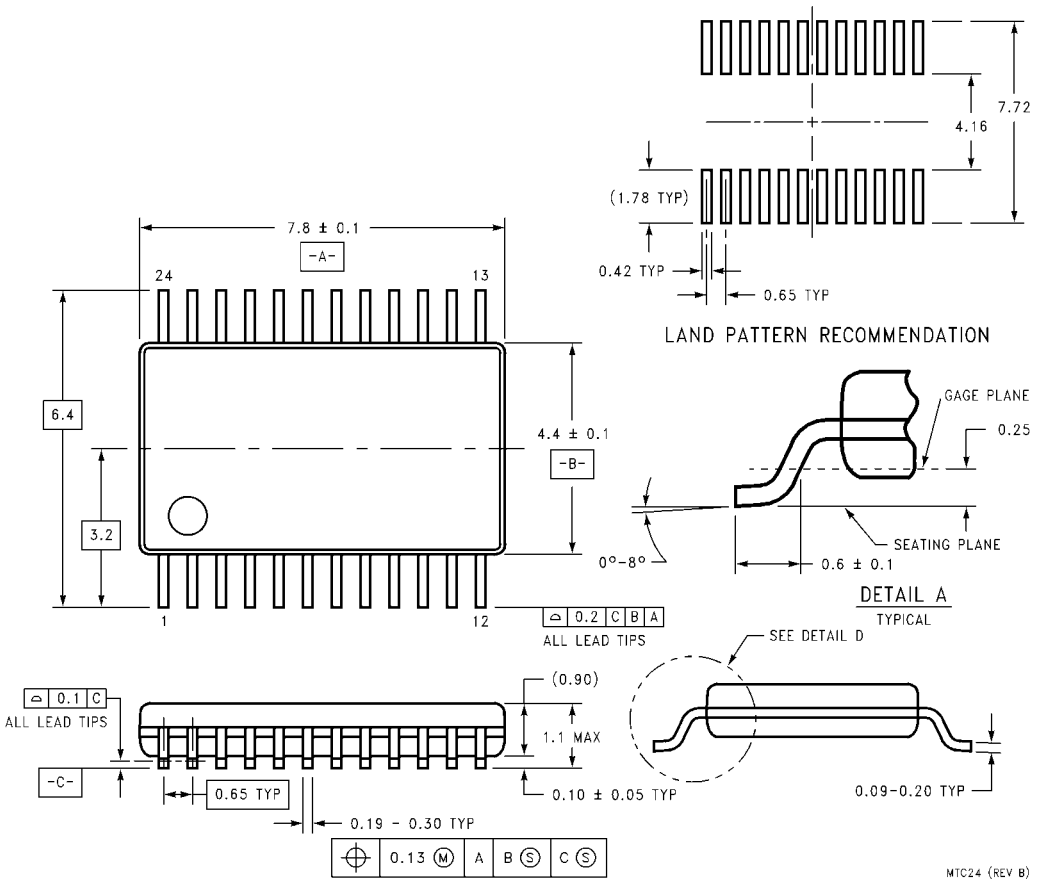


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide
Package Number MQA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC24

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised July 1999

74VCX00
Low Voltage Quad 2-Input NAND Gate with 3.6V Tolerant Inputs and Outputs

General Description

The VCX00 contains four 2-input NAND gates. This product is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The VCX00 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

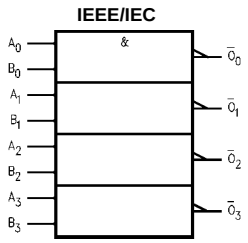
- 1.65V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.8 ns max for 3.0V to 3.6V V_{CC}
  - 3.7 ns max for 2.3V to 2.7V V_{CC}
  - 7.4 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

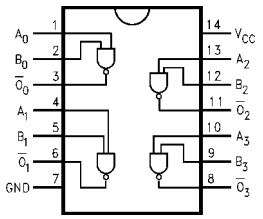
Order Number	Package Number	Package Description
74VCX00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VCX00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
HIGH or LOW State (Note 2)	−0.5V to V_{CC} + 0.5V
V_{CC} = 0V	−0.5V to +4.6V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OL}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per	±100 mA
Supply Pin (I_{CC} or Ground)	
Storage Temperature Range (T_{stg})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
HIGH or LOW State	0V to V_{CC}
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7–3.6		20	µA
		$V_{CC} \leq V_I \leq 3.6V$	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC}$ −0.6V	2.7–3.6		750	µA

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.3	2.0		
		I_{OH} = −12 mA	2.3	1.8		
		I_{OH} = −18 mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le V_I \le 3.6V$	2.3–2.7		±20	

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–2.3	V_{CC} − 0.2		V
		I_{OH} = −6 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \le V_I \le 3.6V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30pF$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay	0.6	2.8	0.8	3.7	1.0	7.4	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 5)		0.5		0.5		0.75	ns

Note 4: For C_L = 50 pF, add approximately 300 ps to the AC maximum specification

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C Typical	Unit
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	T_A = +25°C Typical	Units
C_{IN}	Input Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

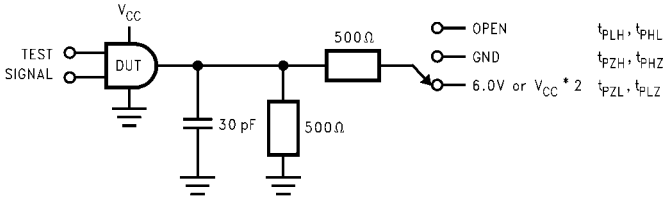


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open

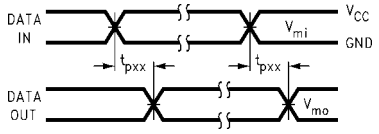
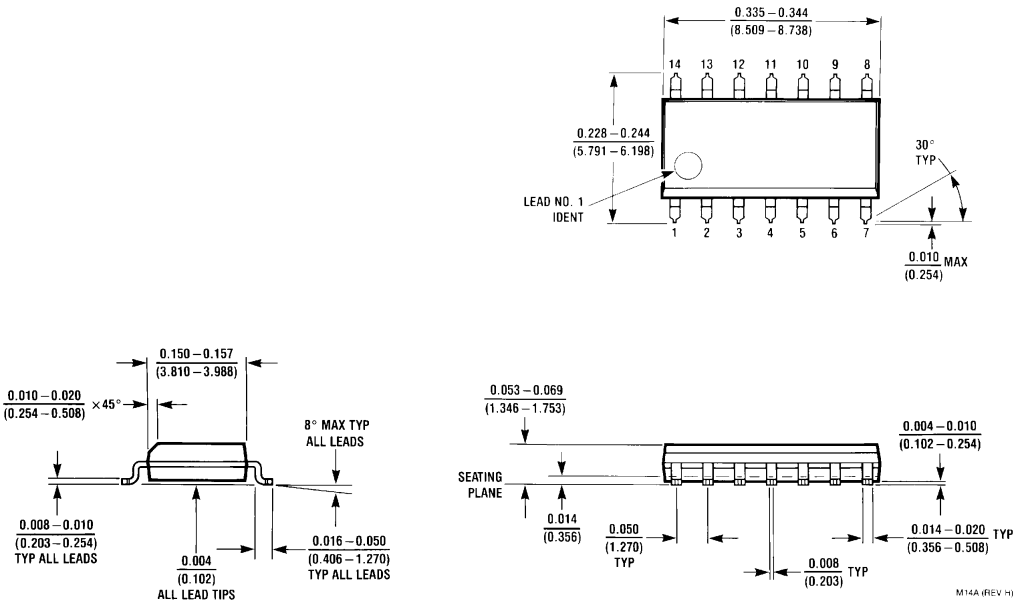


FIGURE 2. Waveform for Inverting and Non-inverting Functions

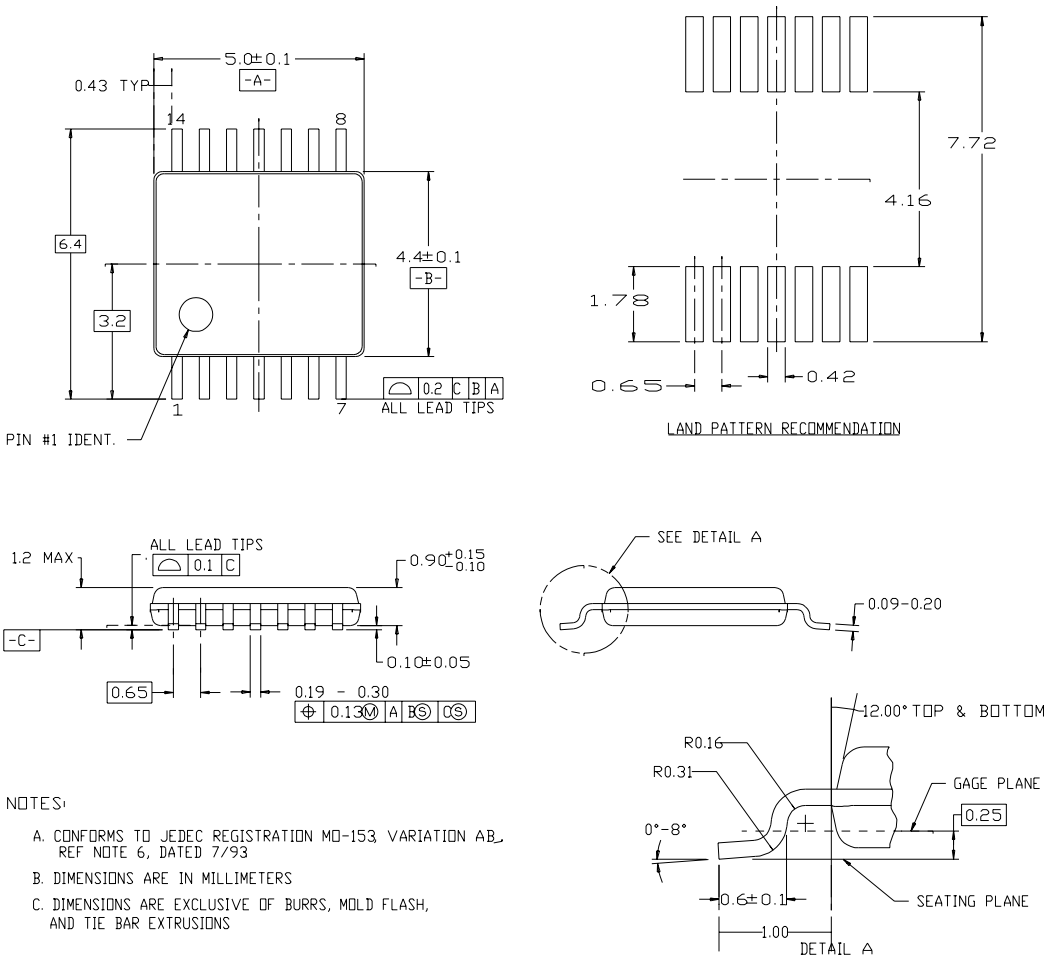
Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

July 1999
Revised July 1999

74VCX08
Low Voltage Quad 2-Input AND Gate with 3.6V Tolerant Inputs and Outputs

General Description

The VCX08 contains four 2-input AND gates. This product is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V

The VCX08 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

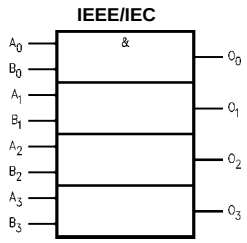
- 1.65V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.8 ns max for 3.0V to 3.6V V_{CC}
  - 3.7 ns max for 2.3V to 2.7V V_{CC}
  - 7.4 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

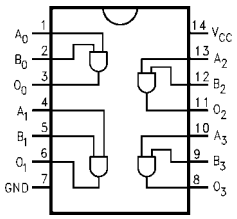
Order Number	Package Number	Package Description
74VCX08M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VCX08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
HIGH or LOW State (Note 2)	−0.5V to V_{CC} +0.5V
V_{CC} = 0V	−0.5V to +4.6V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	+50 mA
DC V_{CC} or Ground Current per	±100 mA
Supply Pin (I_{CC} or Ground)	
Storage Temperature Range (T_{stg})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
HIGH or LOW State	0V to V_{CC}
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{in} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OFF}	Power Off Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ V_I ≤ 3.6V	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.3	2.2		
		I_{OH} = −12 mA	2.3	2.4		
		I_{OH} = −18 mA	2.3	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le V_I \le 3.6V$	2.3–2.7		±20	

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–2.3	V_{CC} − 0.2		V
		I_{OH} = −6 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \le V_I \le 3.6V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30pF$, $R_L = 500\ \Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay	0.6	2.8	0.8	3.7	1.0	7.4	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 5)		0.5		0.5		0.75	ns

Note 4: For C_L = pF, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	−0.25	
			2.5	−0.6	V
			3.3	−0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	T_A = +25°C Typical	Units
C_{IN}	Input Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

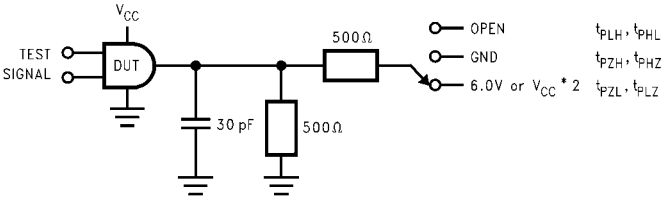


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open

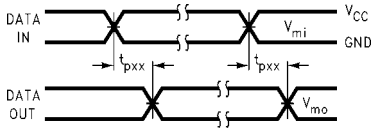
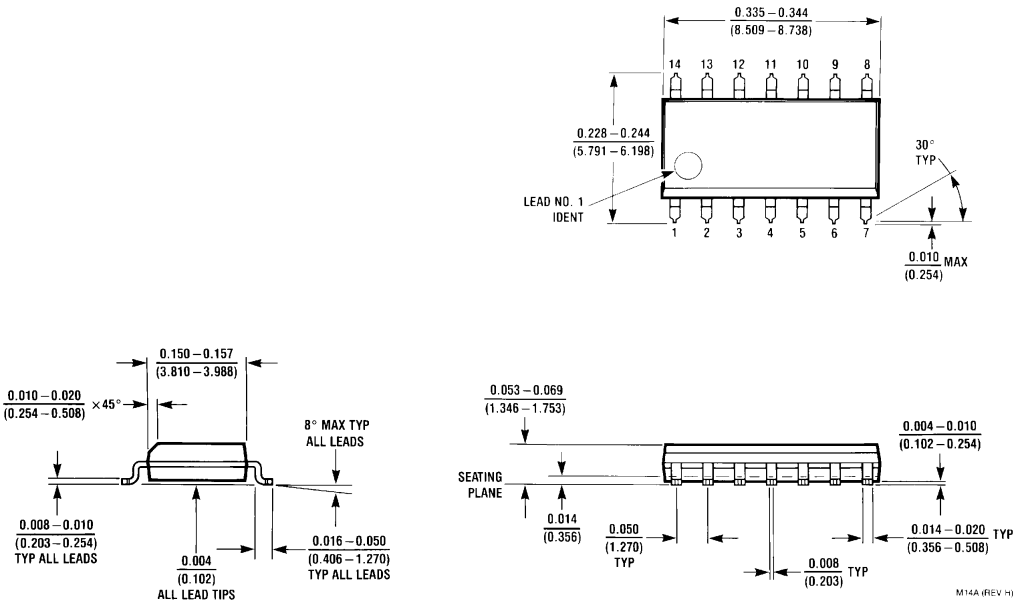


FIGURE 2. Waveform for Inverting and Non-inverting Functions

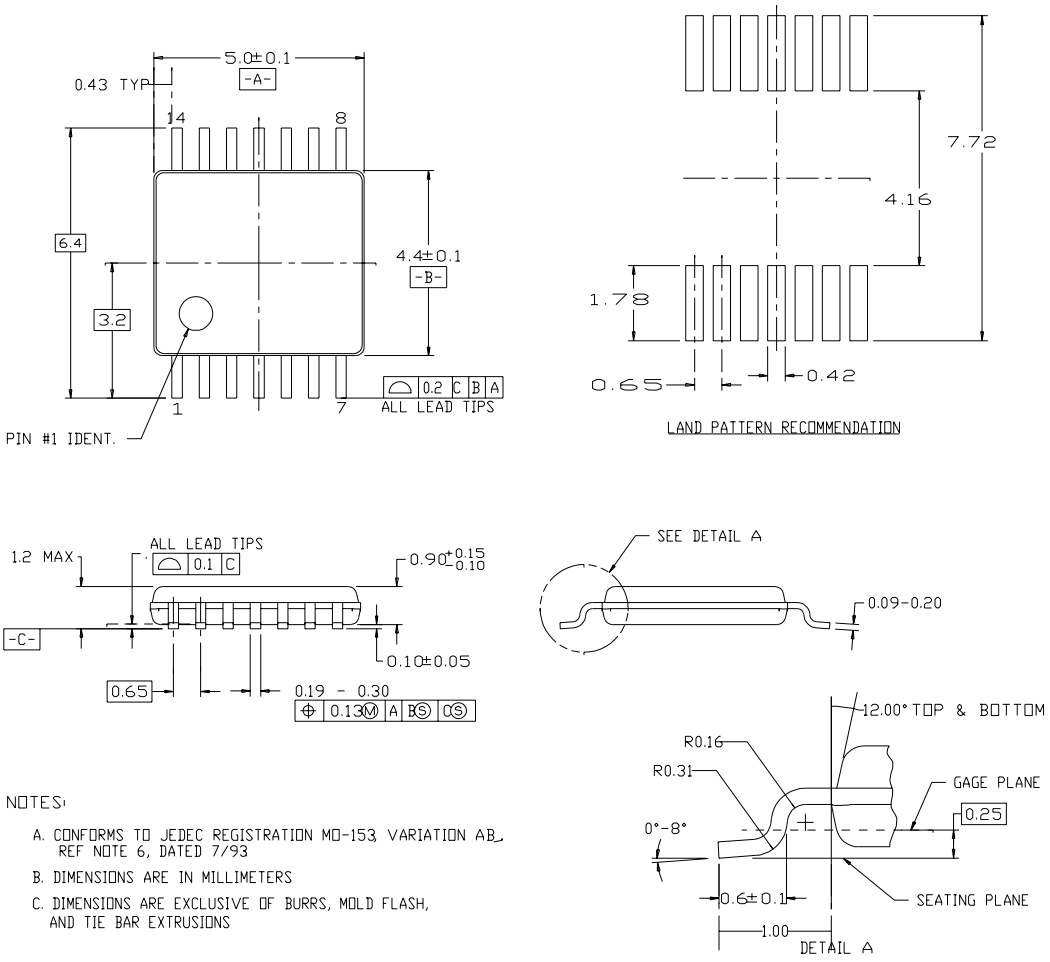
Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised July 1999

74VCX132

Low Voltage Quad 2-Input NAND Gate with Schmitt Trigger Inputs and 3.6V Tolerant Inputs and Outputs

General Description

The VCX132 contains four 2-input NAND gates with Schmitt Trigger Inputs. The pin configuration and function are the same as the VCX00 except the inputs have hysteresis between the positive-going and negative-going input thresholds. This hysteresis is useful for transforming slowly switching input signals into sharply defined, jitter-free output signals. This product should be used where noise margin greater than that of conventional gates is required.

The VCX132 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

This product is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

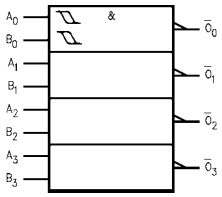
- 1.65V-3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 4.1 ns max for 2.3V to 2.7V V_{CC}
  - 8.2 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

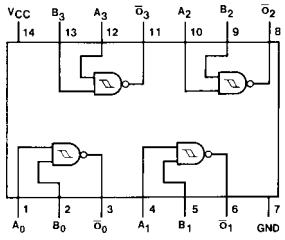
Order Number	Package Number	Package Description
74VCX132M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VCX132MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Diagram



Connection Diagram



Pin Descriptions

Pin Name	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to 4.6V
DC Output Voltage (V_O)	
HIGH or LOW State (Note 2)	−0.5V to V_{CC} + 0.5V
V_{CC} = 0V	−0.5V to +4.6V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
HIGH or LOW State	0V to V_{CC}
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{t+}	Positive Threshold		3.6		2.2	V
			3.0		2.0	
V_{t-}	Negative Threshold		3.6	0.8		V
			3.0	0.7		
V_H	Input Hysteresis		3.6	0.3	1.2	V
			3.0	0.3	1.2	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC}–0.2		V
		I_{OH}= −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 µA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±15.0	µA
I_{OFF}	Power Off Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ V_I ≤ 3.6V	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

DC Electrical Characteristics ($2.3V \leq V_{CC} \leq 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{t+}	Positive Threshold		2.3		1.6	V
V_{t-}	Negative Threshold		2.3	0.5		V
ΔV_T	Input Hysteresis		2.3	0.3	1.0	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC}-0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12\ \mu A$	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.3–2.7		±5.0	μA
I_{OFF}	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \leq V_I \leq 3.6V$	2.3–2.7		±20	

DC Electrical Characteristics ($1.65V \leq V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{t+}	Positive Threshold		1.65		1.3	V
V_{t-}	Negative Threshold		1.65	0.25		V
ΔV_T	Input Hysteresis		1.65	0.2	0.9	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65–2.3	$V_{CC}-0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65–2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	1.65–2.3		±5.0	μA
I_{OFF}	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	μA
		$V_{CC} \leq V_I \leq 3.6V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3\ V \pm 0.3V$		$V_{CC} = 2.5\ V \pm 0.2V$		$V_{CC} = 1.8\ V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	0.6	3.3	0.8	4.1	1.0	8.2	ns
t_{PLH}								
t_{OSHL}	Output to Output		0.5		0.5		0.75	ns
t_{OSLH}	Skew (Note 5)							

Note 4: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

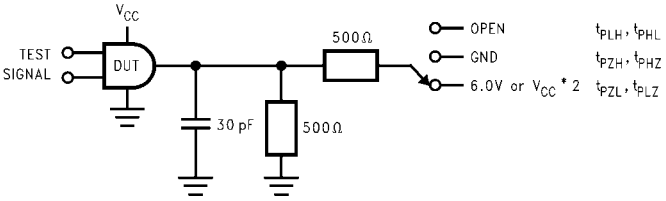


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open

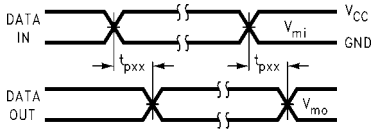
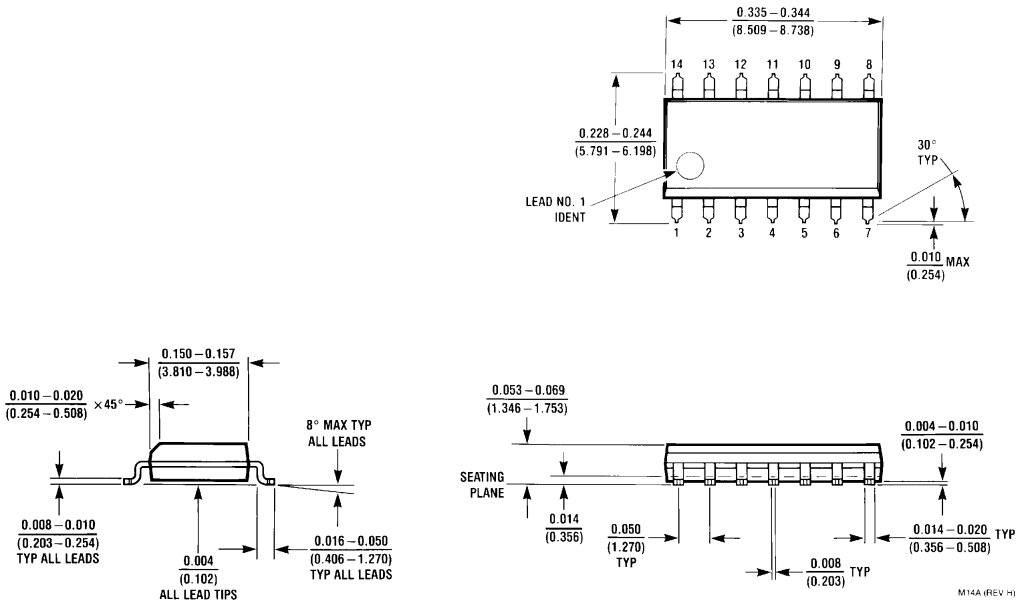


FIGURE 2. Waveform for Inverting and Non-inverting Functions

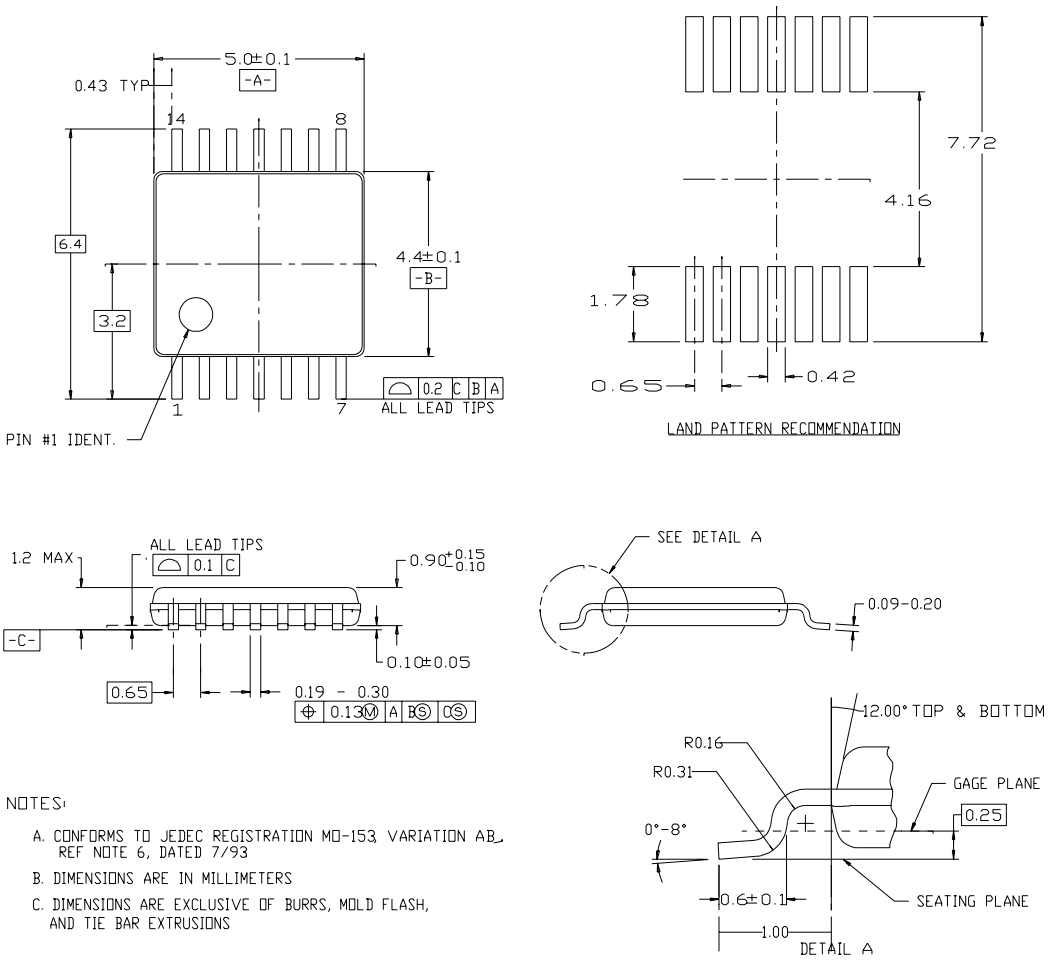
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

FAIRCHILD SEMICONDUCTOR™

January 1998
Revised April 1999

74VCX162240

Low Voltage 16-Bit Inverting Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in Outputs

General Description

The VCX162240 contains sixteen inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX162240 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The 74VCX162240 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD}
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 3.8 ns max for 2.3V to 2.7V V_{CC}
  - 7.6 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

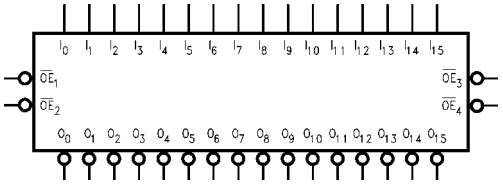
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX162240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JECED MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

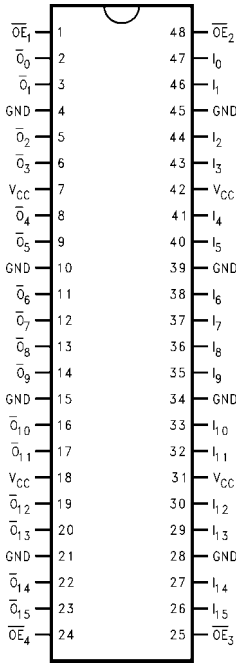
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

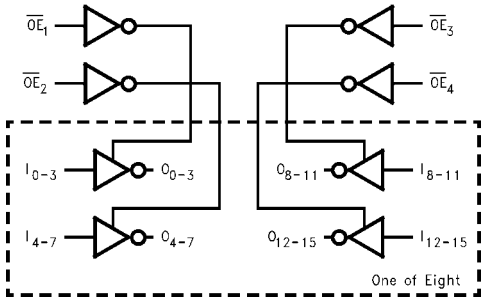
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162240 contains sixteen inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.80	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} − 0.2		V
		I_{OH} = −4 mA	2.3	2.0		V
		I_{OH} = −6 mA	2.3	1.8		V
		I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 6 mA	2.3		0.4	V
		I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} − 0.2		V
		I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.3	1.0	3.8	1.5	7.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	5.1	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.6	1.0	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

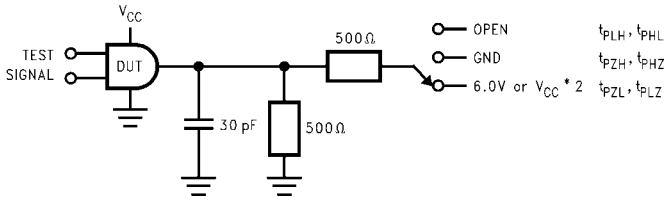
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC}	$T_A = +25°C$	Units
			(V)	Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	
			2.5	–0.25	V
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

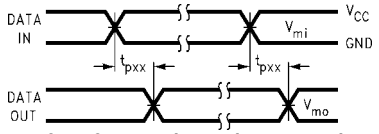


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

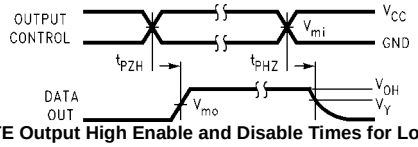


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

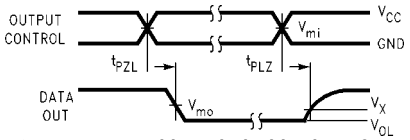
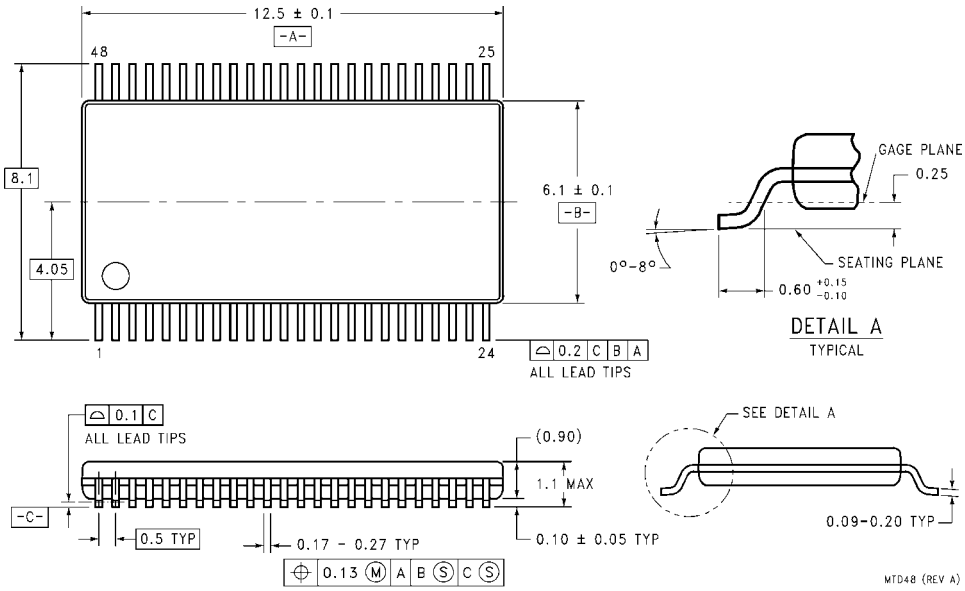


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

August 1997
Revised April 1999

74VCX162244

Low Voltage 16-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistor in Outputs

General Description

The VCX162244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX162244 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The 74VCX162244 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD}
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 3.8 ns max for 2.3V to 2.7V V_{CC}
  - 7.6 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

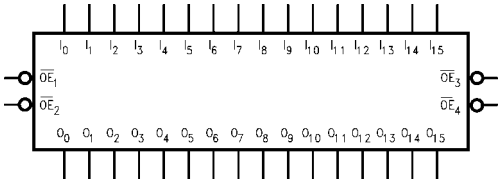
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX162244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

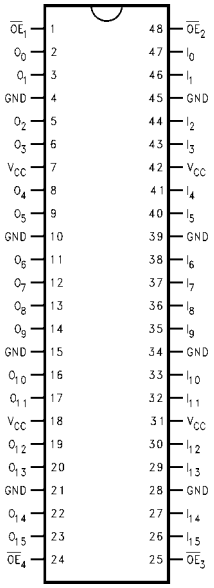
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

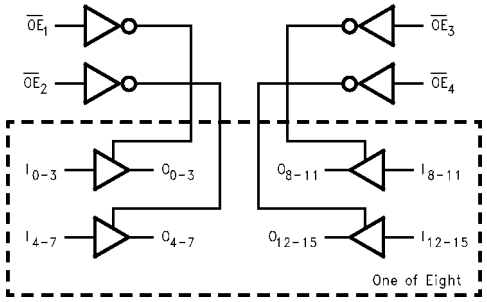
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \leq V_{CC} \leq 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -4$ mA	2.3	2.0		V
		$I_{OH} = -6$ mA	2.3	1.8		V
		$I_{OH} = -8$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	2.3–2.7		0.2	V
		$I_{OL} = 6$ mA	2.3		0.4	V
		$I_{OL} = 8$ mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 6)	2.3–2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \leq V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65-2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65-2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	1.65-2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	1.65-2.3		0.2	V
		$I_{OL} = 3$mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	1.65-2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65-2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65-2.3		20	µA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 7)	1.65-2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.3	1.0	3.8	1.5	7.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	5.1	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.6	1.0	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

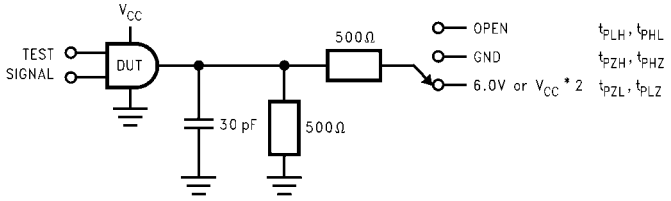
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC}	$T_A = +25°C$	Units
			(V)	Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	
			2.5	–0.25	V
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8 ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

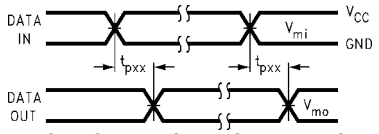


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

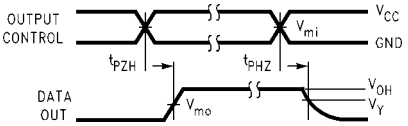


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

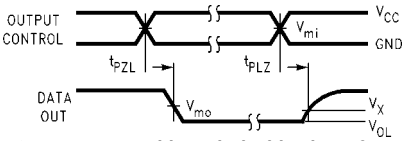
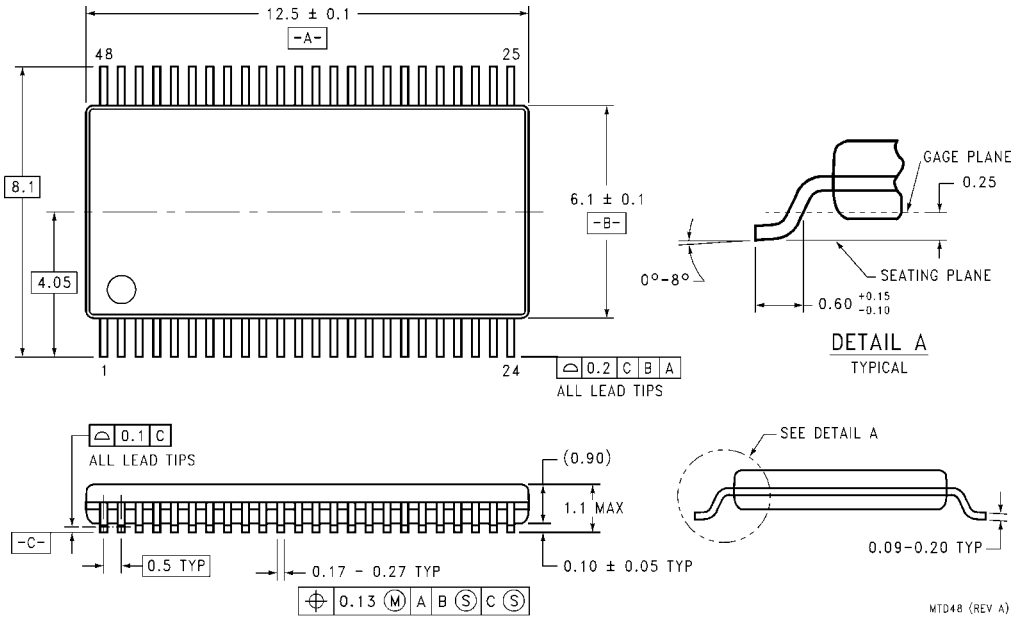


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

October 1996
Revised April 1999

74VCX162245

Low Voltage 16-Bit Bidirectional Transceiver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in A Port Outputs

General Description

The VCX162245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The 74VCX162245 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX162245 is also designed with 26Ω series resistance in the A Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in A port outputs
- t_{PD} (B to A)
  - 3.4 ns max for 3.0V to 3.6V V_{CC}
  - 4.3 ns max for 2.3V to 2.7V V_{CC}
  - 8.6 ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL} A outputs)
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

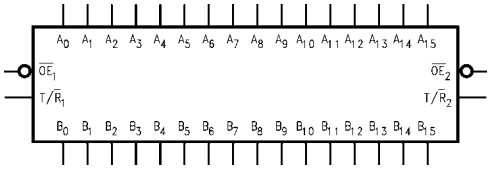
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX162245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

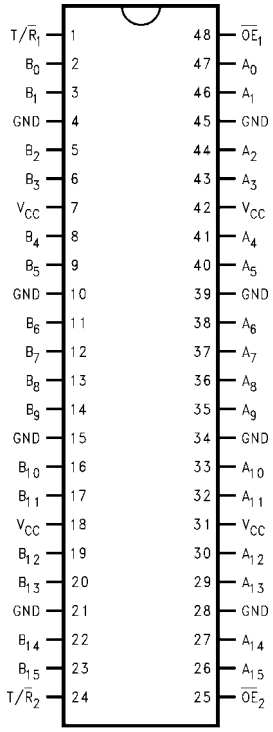
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input
T/$\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

Connection Diagram



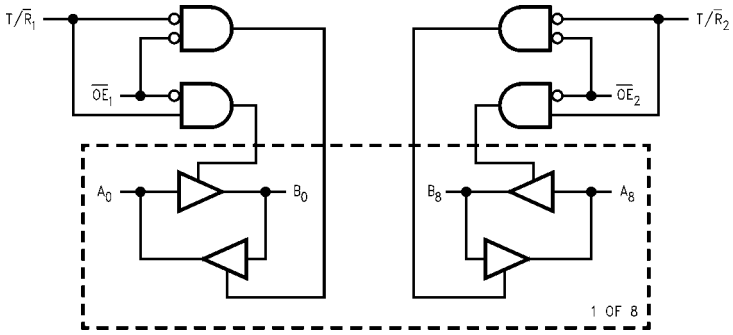
Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH Z State on A_8–A_{15}, B_8–B_{15}

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs and I/O's may not float)
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-State	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}-A Outputs	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 1.95V	±3 mA
Output Current in ± I_{OH}/I_{OL}-B Outputs	
V_{CC} = 3.0V to 3.6V	± 24mA
V_{CC} = 2.3V to 2.7V	± 18mA
V_{CC} = 1.65V to 2.3V	±6mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (Δt/ΔV)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused pins (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		
	A Outputs	I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		
		I_{OH} = −12 mA	3.0	2.2		
	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		
	B Outputs	I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	
	A Outputs	I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12 mA	3.0		0.8	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	
	B Outputs	I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
	A Outputs	$I_{OH} = -4$ mA	2.3	2.0		
		$I_{OH} = -6$ mA	2.3	1.8		
		$I_{OH} = -8$ mA	2.3	1.7		
	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
	B Outputs	$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
	A Outputs	$I_{OL} = 6$ mA	2.3		0.4	
		$I_{OL} = 8$ mA	2.3		0.6	
	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
	B Outputs	$I_{OL} = 12$ mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3–2.7		±20	

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65-2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65-2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65-2.3	$V_{CC} - 0.2$		V
	A Outputs	$I_{OH} = -3$ mA	1.65	1.4		
	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65-2.3	$V_{CC} - 0.2$		V
	B Outputs	$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65-2.3		0.2	V
	A Outputs	$I_{OL} = 3$ mA	1.65		0.3	
	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65-2.3		0.2	V
	B Outputs	$I_{OL} = 6$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65-2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65-2.3		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65-2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65-2.3		±20	

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay, A to B	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PHL}, t_{PLH}	Prop Delay, B to A	0.8	3.4	1.0	4.3	1.5	8.6	ns
t_{PZL}, t_{PZH}	Output Enable Time, A to B	0.8	3.8	1.0	4.9	1.5	9.3	ns
t_{PZL}, t_{PZH}	Output Enable Time, B to A	0.8	4.2	1.0	5.7	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time, A to B	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_{PLZ}, t_{PHZ}	Output Disable Time, B to A	0.8	4.1	1.0	4.8	1.5	8.6	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.25 0.6 0.8	V
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.15 0.25 0.35	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	–0.25 –0.6 –0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.15 –0.25 –0.35	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.5 1.9 2.2	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.55 2.05 2.65	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V, or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
$C_{I/O}$	Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

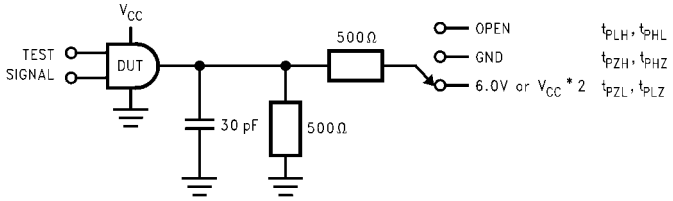


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

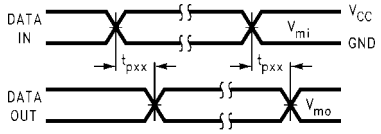


FIGURE 2. Waveform for Inverting and Non-inverting Functions

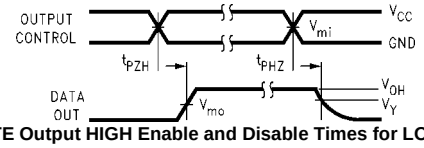


FIGURE 3. 3-STATE Output HIGH Enable and Disable Times for LOW Voltage Logic

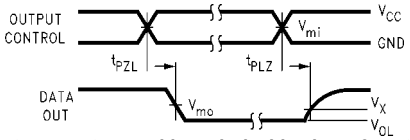
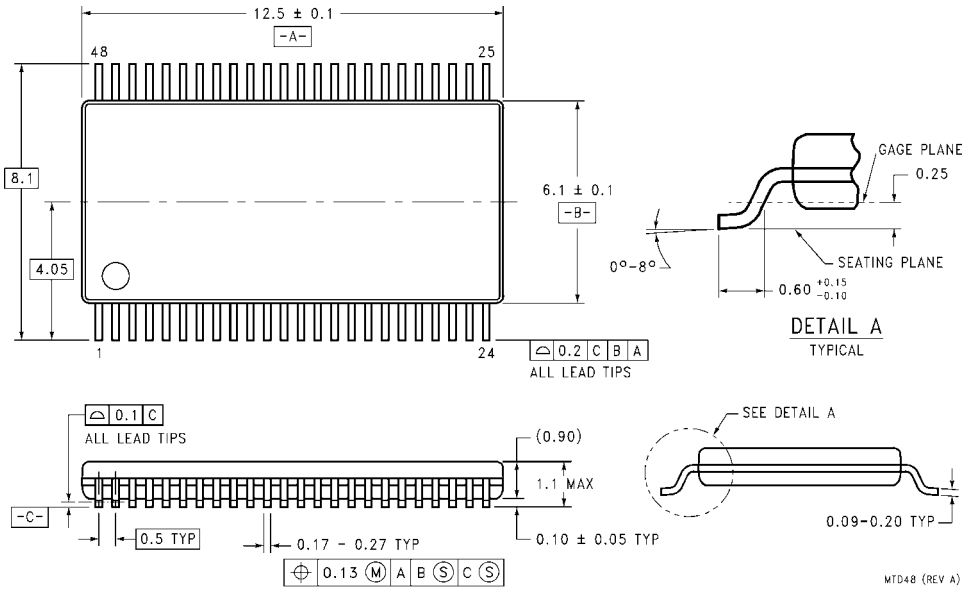


FIGURE 4. 3-STATE Output LOW Enable and Disable Times for LOW Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74VCX162373
Low Voltage 16-Bit Transparent Latch with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in Outputs

General Description

The VCX162373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear to be transparent to the data when the Latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The VCX162373 is also designed with 26Ω resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers and bus transceivers/transmitters.

The 74VCX162373 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX162373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD} (I_n to O_n)
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 4.5 ns max for 2.3V to 2.7V V_{CC}
  - 9.0 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Support live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

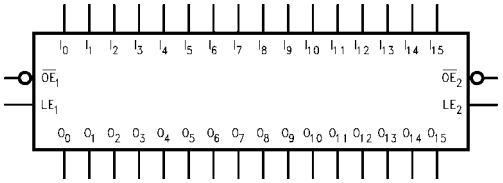
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Ordering Number	Package Number	Package Description
74VCX162373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

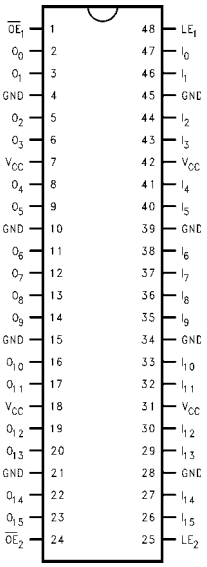
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

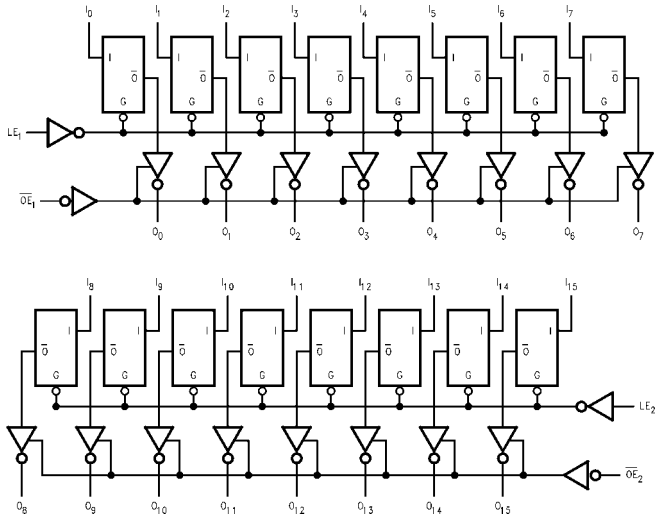
Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCX162373 contains sixteen edge D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition on LE_n. The 3-STATE outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} − 0.2		V
		I_{OH} = −4 mA	2.3	2.0		V
		I_{OH} = −6 mA	2.3	1.8		V
		I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 6 mA	2.3		0.4	V
		I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} − 0.2		V
		I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 – 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n	0.8	3.3	1.0	4.5	1.5	9.0	ns
t_{PHL}, t_{PLH}	Prop Delay LE to O_n	0.8	3.6	1.0	4.9	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.9	1.0	5.4	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.0	1.0	4.4	1.5	7.9	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

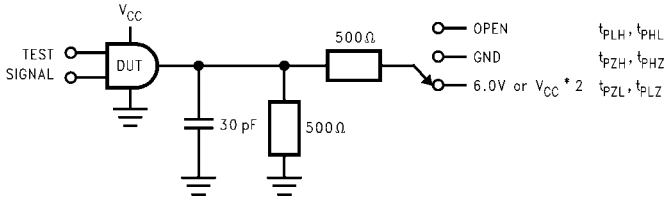
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	V
			2.5	0.25	
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.15	V
			2.5	−0.25	
			3.3	−0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	V
			2.5	2.05	
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

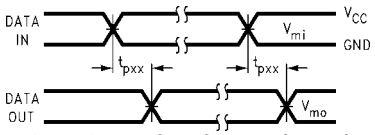


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

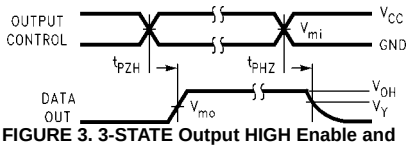


FIGURE 3. 3-STATE Output HIGH Enable and Disable Times for Low Voltage Logic

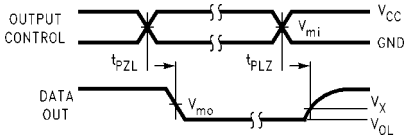


FIGURE 4. 3-STATE Output LOW Enable and Disable Times for Low Voltage Logic

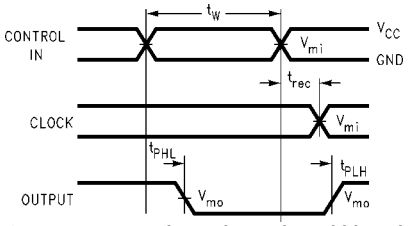


FIGURE 5. Propagation Delay, Pulse Width and t_{REC} Waveforms

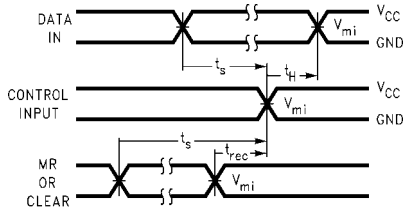
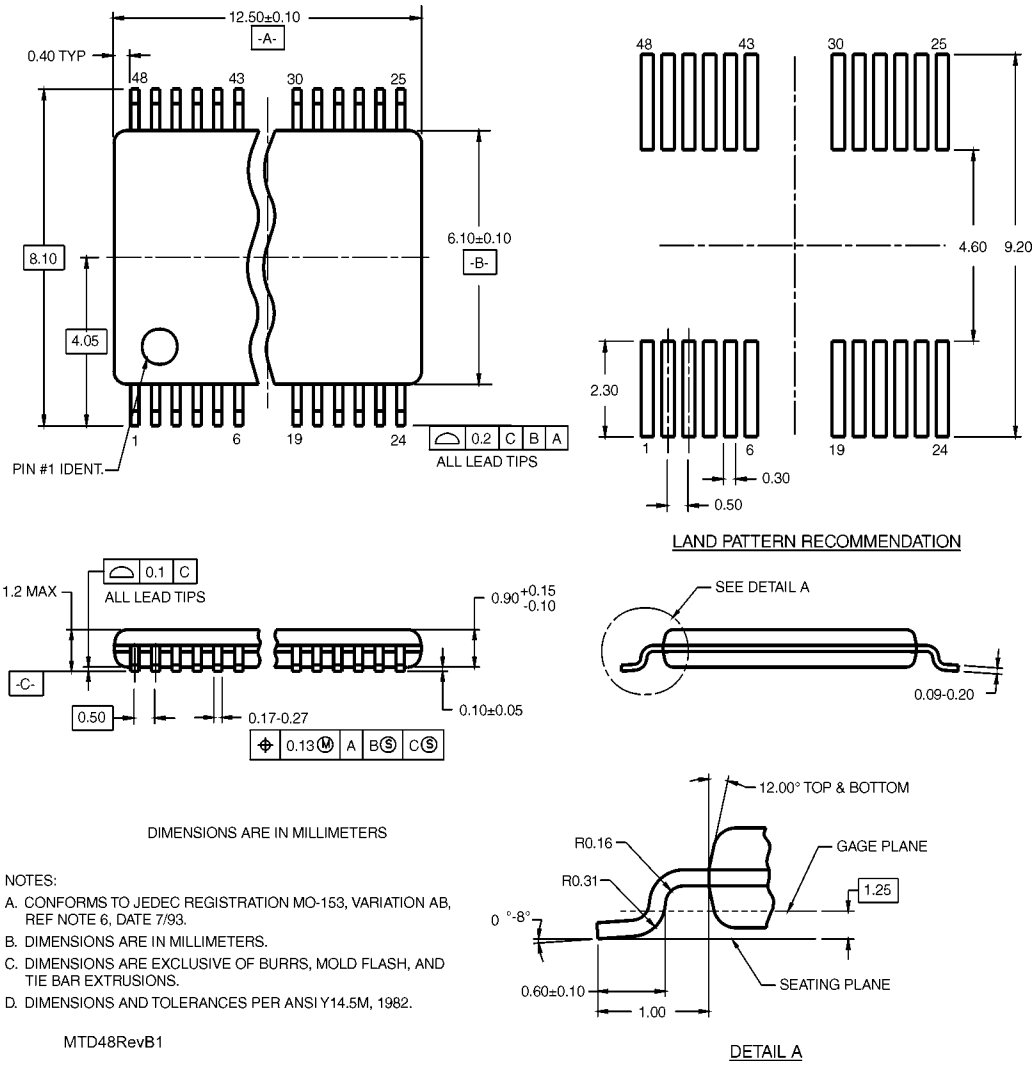


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74VCX162374
Low Voltage 16-Bit D-Type Flip-Flop with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in Outputs

General Description

The VCX162374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and output enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

The VCX162374 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers and bus transceivers/transmitters.

The 74VCX162374 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX162374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD} (CLK to O_n)
  - 3.4 ns max for 3.0V to 3.6V V_{CC}
  - 4.8 ns max for 2.3V to 2.7V V_{CC}
  - 9.6 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

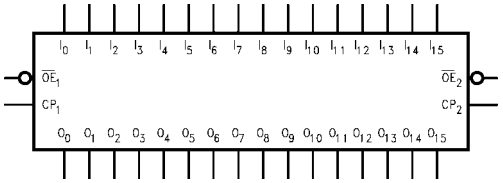
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX162374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

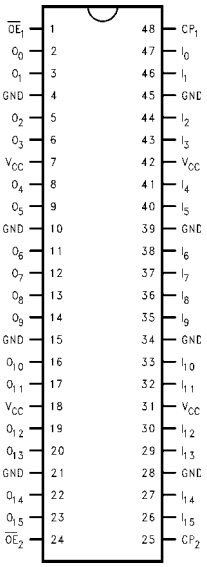
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
⌐	L	H	H
⌐	L	L	L
L	L	X	O_0
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
⌐	L	H	H
⌐	L	L	L
L	L	X	O_0
X	H	X	Z

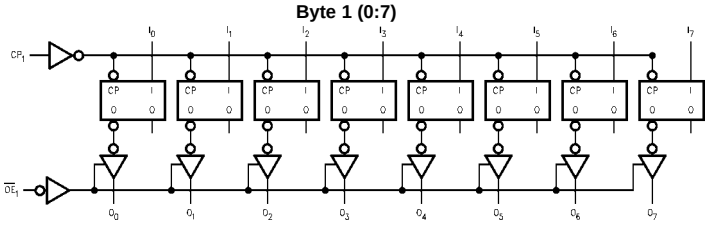
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of CP

Functional Description

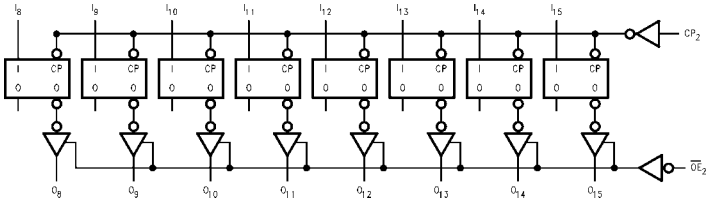
The 74VCX162374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each clock has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual I inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operations of the $\overline{OE}_n$ input does not affect the state of the flip-flops.

Logic Diagram

Byte 1 (0:7)



Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	2.3 – 2.7	V_{CC} − 0.2		V
		I_{OH} = −4 mA	2.3	2.0		V
		I_{OH} = −6 mA	2.3	1.8		V
		I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	2.3 – 2.7		0.2	V
		I_{OL} = 6 mA	2.3		0.4	V
		I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	μA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	1.65 - 2.3	V_{CC} − 0.2		V
		I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	1.65 - 2.3		0.2	V
		I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	μA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay CP to O_n	0.8	3.4	1.0	4.8	1.5	9.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.9	1.0	5.4	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.0	1.0	4.4	1.5	7.9	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

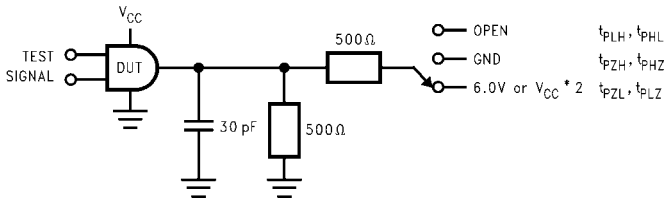
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	V
			2.5	0.25	
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.15	V
			2.5	−0.25	
			3.3	−0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	V
			2.5	2.05	
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

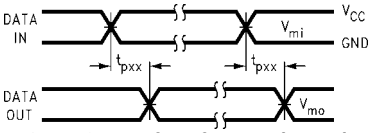


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

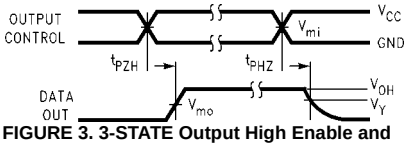


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

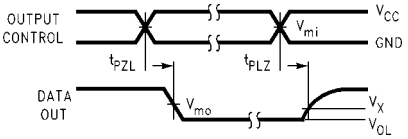


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

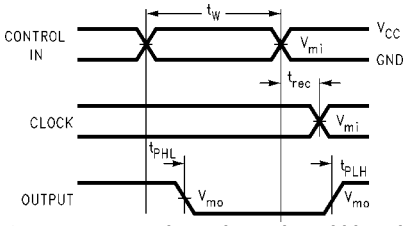


FIGURE 5. Propagation Delay, Pulse Width and t_{REC} Waveforms

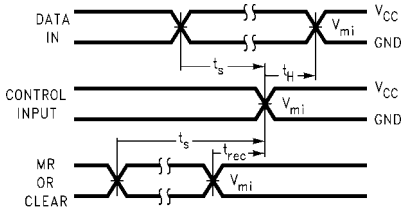
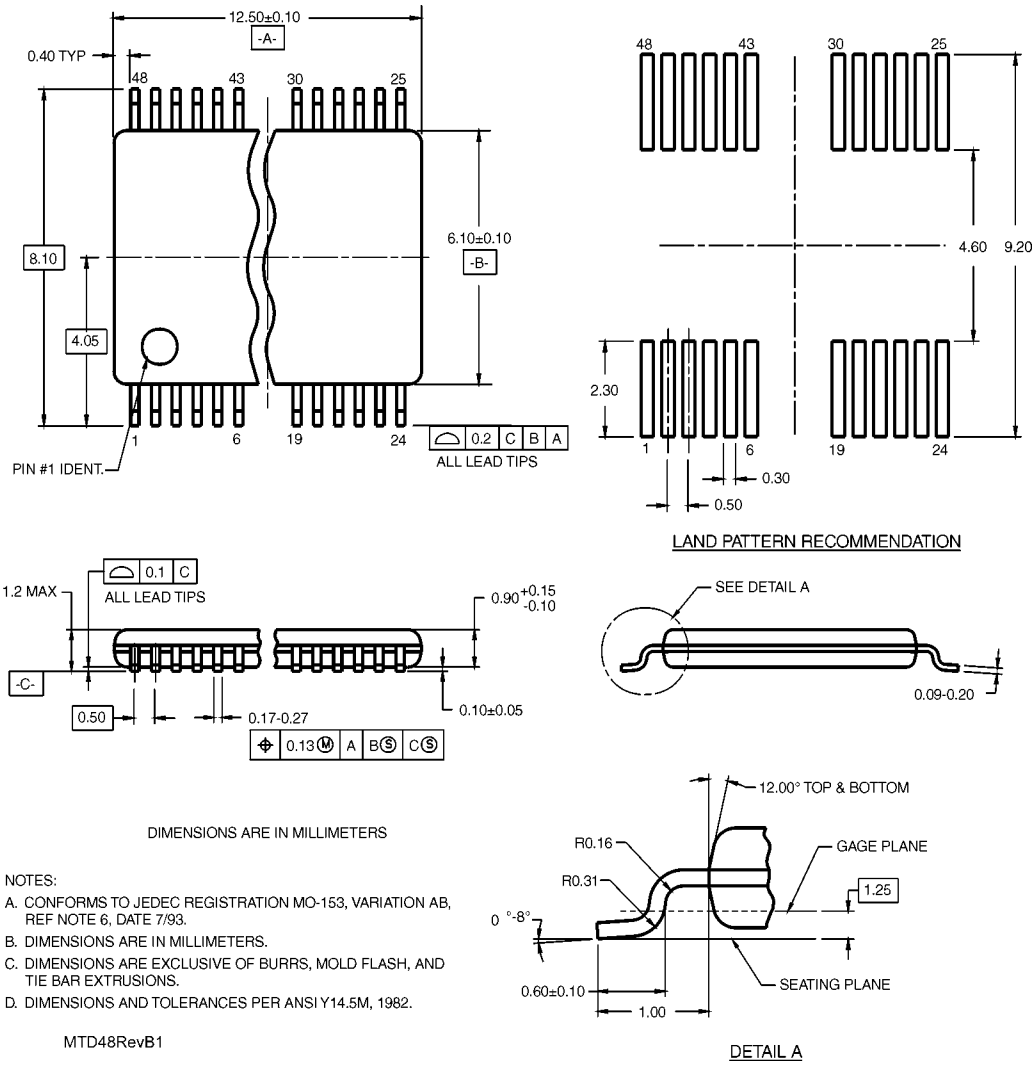


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Body Width
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1998
Revised April 1999

74VCX16240
Low Voltage 16-Bit Inverting Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16240 contains sixteen inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX16240 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.5 ns max for 3.0V to 3.6V V_{CC}
  - 3.0 ns max for 2.3V to 2.7V V_{CC}
  - 6.0 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

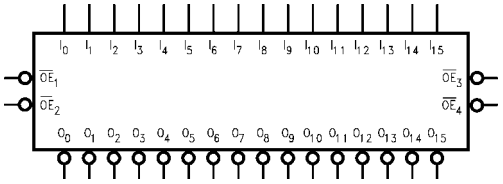
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

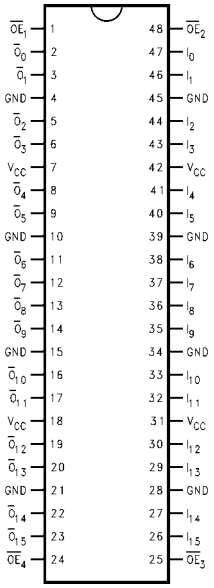
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

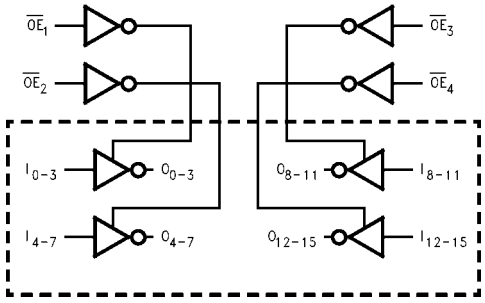
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX16240 contains sixteen inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	2.7 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	μA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	μA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	μA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	μA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	μA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	μA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = –6 mA	2.3	2.0		V
		I_{OH} = –12 mA	2.3	1.8		V
		I_{OH} = –18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = –6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 – 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.1	1.5	8.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	7.6	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

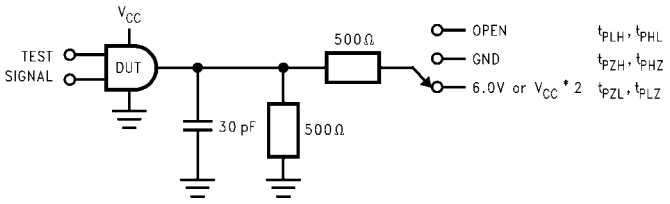
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

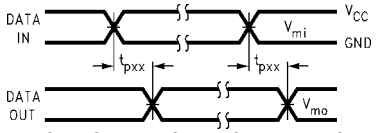


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

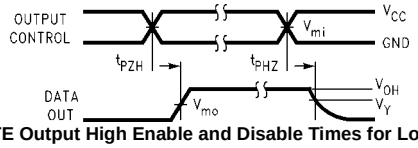


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

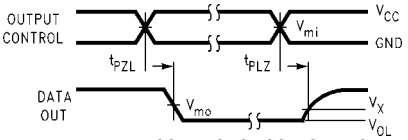
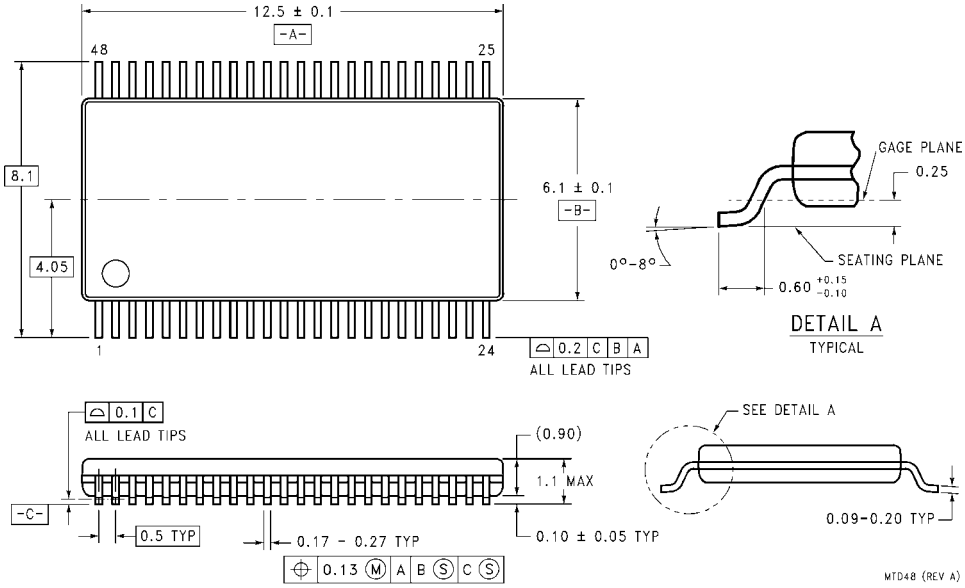


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

October 1996
Revised April 1999

74VCX16244

Low Voltage 16-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX16244 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.5 ns max for 3.0V to 3.6V V_{CC}
  - 3.0 ns max for 2.3V to 2.7V V_{CC}
  - 6.0 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.8V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

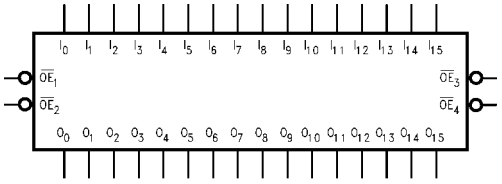
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

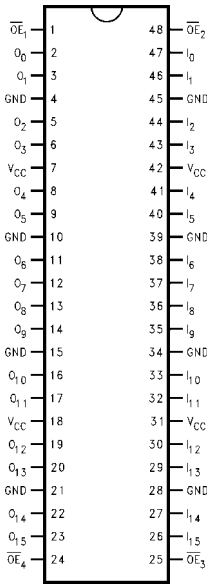
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8-I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4-I_7	O_4-O_7
L	L	L
L	H	H
H	X	Z

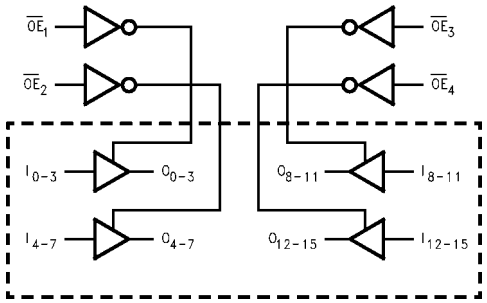
Inputs		Outputs
$\overline{OE}_4$	I_{12}-I_{15}	O_{12}-O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX16244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7–3.6		20	µA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 5)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC}$ −0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		V
		$I_{OH} = -12$ mA	2.3	1.8		V
		$I_{OH} = -18$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	V
		$I_{OL} = 18$ mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3–2.7		±20	μA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65–2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65–2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65–2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65–2.3		±20	μA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.1	1.5	8.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

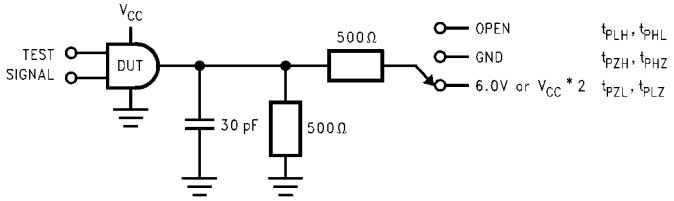
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

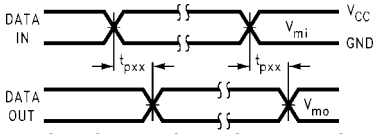


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

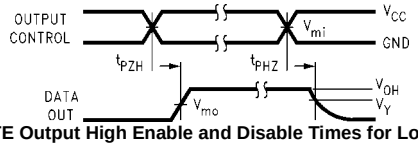


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

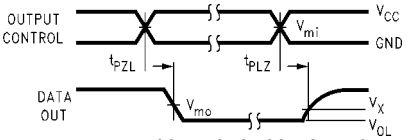
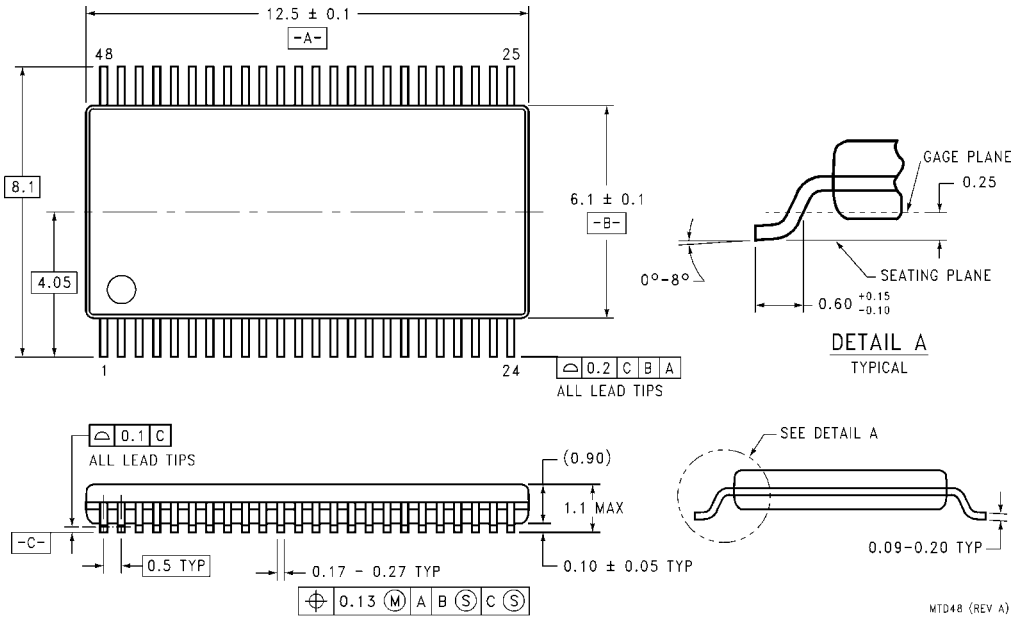


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

October 1996
Revised April 1999

74VCX16245
Low Voltage 16-Bit Bidirectional Transceiver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation. The T/$\overline{R}$ inputs determine the direction of data flow through the device. The $\overline{OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

The 74VCX16245 is designed for low voltage (1.65 to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.5 ns max for 3.0V to 3.6V V_{CC}
  - 3.0 ns max for 2.3V to 2.7V V_{CC}
  - 6.0 ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

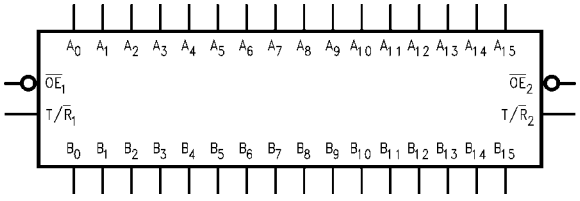
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

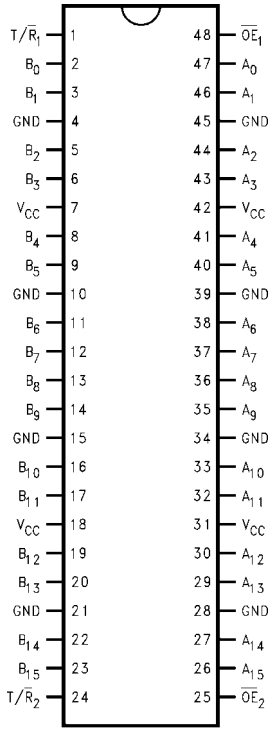
Order Number	Package Number	Package Description
74VCX16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

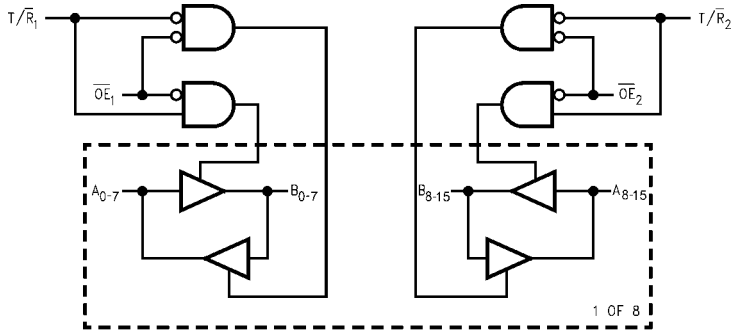
Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH Z State on A_8–A_{15}, B_8–B_{15}

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs and I/O's may not float)
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3–2.7		±20	

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65-2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65-2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65-2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65-2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65-2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65-2.3		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65-2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65-2.3		±20	

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	4.9	1.5	9.3	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_{OSHL}	Output to Output		0.5		0.5		0.75	ns
t_{OSLH}	Skew (Note 9)							

Note 8: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V, or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
$C_{I/O}$	Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, F = 10 MHz $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

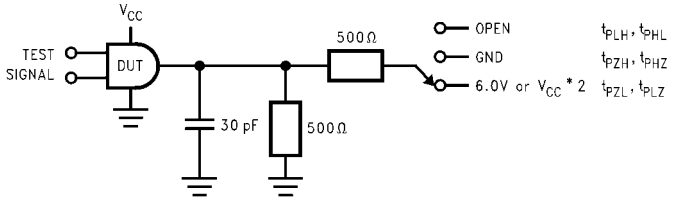


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

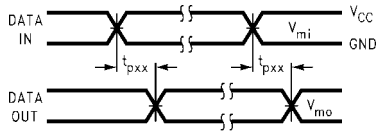


FIGURE 2. Waveform for Inverting and Non-inverting Functions

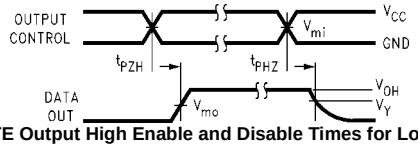


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

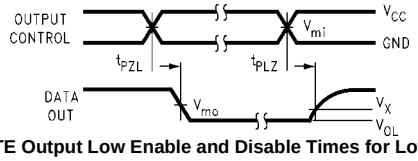
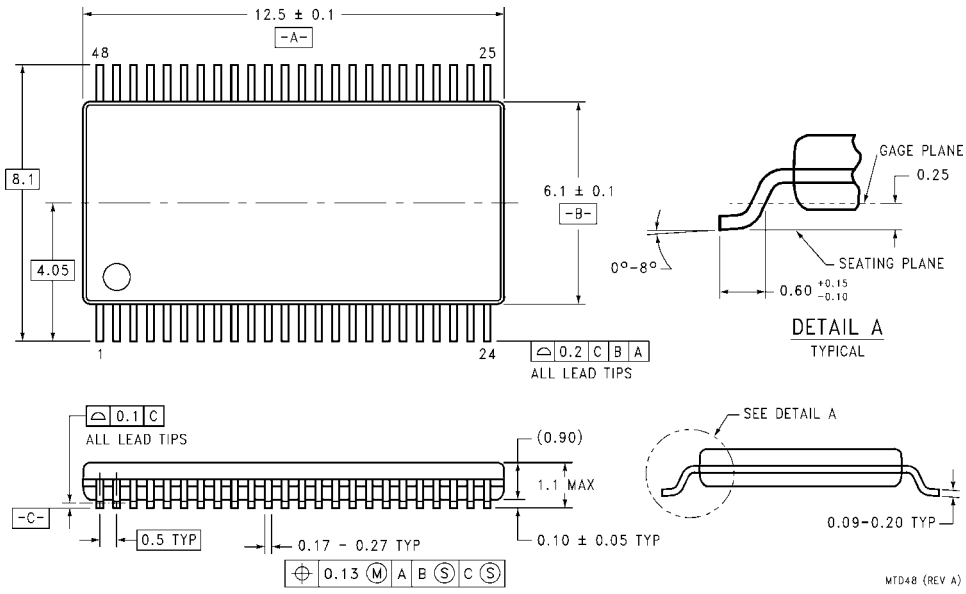


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

April 1998
Revised April 1999

74VCX162601

Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in the B-Port Outputs

General Description

The VCX162601, 18-bit universal bus transceiver, combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable ($\overline{OEAB}$ and $\overline{OEBA}$), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable ($\overline{CLKENAB}$ and $\overline{CLKENBA}$) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH-to-LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. Output-enable $\overline{OEAB}$ is active-LOW. When $\overline{OEAB}$ is HIGH, the outputs are in the HIGH-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, LEBA, CLKBA and $\overline{CLKENBA}$.

The 74VCX162601 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The VCX162601 is also designed with 26Ω series resistors in the B-Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in B-Port outputs
- t_{PD} (A to B)
  - 3.8 ns max for 3.0V to 3.6V V_{CC}
  - 4.6 ns max for 2.3V to 2.7V V_{CC}
  - 9.2 ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL} B outputs)
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

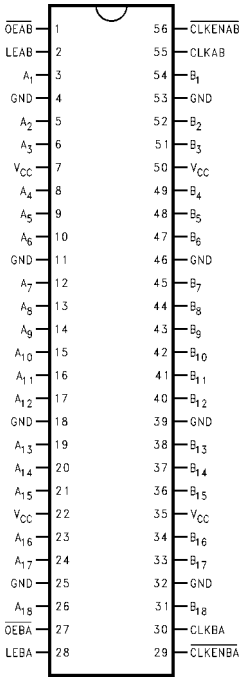
Order Number	Package Number	Package Description
74VCX162601MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
$\overline{CLKENAB}$, $\overline{CLKENBA}$	Clock Enable Inputs
A_1–A_{18}	Side A Inputs or 3-STATE Outputs
B_1–B_{18}	Side B Inputs or 3-STATE Outputs

Connection Diagram



Function Table (Note 2)

Inputs					Outputs
$\overline{CLKENAB}$	$\overline{OEAB}$	LEAB	CLKAB	A_n	B_n
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	B_0 (Note 3)
H	L	L	X	X	B_0 (Note 3)
L	L	L	↑	L	L
L	L	L	↑	H	H
L	L	L	L	X	B_0 (Note 3)
L	L	L	H	X	B_0 (Note 4)

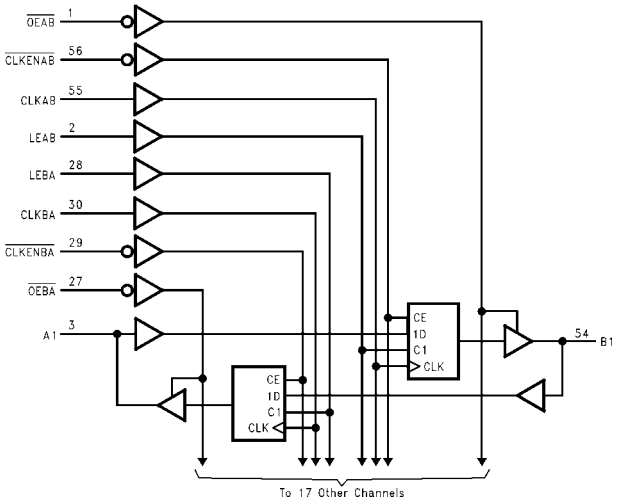
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{OEBA}$, LEBA, CLKBA, and $\overline{CLKENBA}$.

Note 3: Output level before the indicated steady-state input conditions were established.

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings (Note 5)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-State	−0.5V to +4.6V
Outputs Active (Note 6)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL} B Outputs	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 1.95V	±3 mA
Output Current in $\pm I_{OH}/I_{OL}$ A Outputs	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 5: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
	B Outputs	I_{OH} = −6 mA	2.7	2.2		
		I_{OH} = −8 mA	3.0	2.4		
		I_{OH} = −12 mA	3.0	2.2		
	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
	A Outputs	I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
	B Outputs	I_{OL} = 6 mA	2.7		0.4	
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12 mA	3.0		0.8	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
	A Outputs	I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7 – 3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 8)	2.7 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7 – 3.6		750	µA

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 2.7	V_{CC} – 0.2		V
	B Outputs	I_{OH} = –4 mA	2.3	2.0		
		I_{OH} = –6 mA	2.3	1.8		
		I_{OH} = –8 mA	2.3	1.7		
	HIGH Level Output Voltage	I_{OH} = – 100µA	2.3 – 2.7	V_{CC} – 0.2		V
	A Outputs	I_{OH} = –6 mA	2.3	2.0		
		I_{OH} = –12 mA	2.3	1.8		
		I_{OH} = –18 mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
	B Outputs	I_{OL} = 6 mA	2.3		0.4	
		I_{OL} = 8 mA	2.3		0.6	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
	A Outputs	I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3 – 2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 9)	2.3 – 2.7		±20	

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
	B Outputs	I_{OH} = –3 mA	1.65	1.4		
	HIGH Level Output Voltage	$_{OH}$ = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
	A Outputs	I_{OH} = –6 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
	B Outputs	I_{OL} = 3 mA	1.65		0.3	
	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
	A Outputs	I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 10)	1.65 - 2.3		±20	

Note 10: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 11)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Propagation Delay B to A	0.8	2.9	1.0	3.5	1.5	7.0	ns
t_{PHL}, t_{PLH}	Propagation Delay A to B	0.8	3.8	1.0	4.6	1.5	9.2	ns
t_{PHL}, t_{PLH}	Propagation Delay Clock to A	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PHL}, t_{PLH}	Propagation Delay Clock to B	0.8	4.4	1.0	5.5	1.5	9.8	ns
t_{PHL}, t_{PLH}	Propagation Delay LEBA to A	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PHL}, t_{PLH}	Propagation Delay LEAB to B	0.8	4.4	1.0	5.8	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time $\overline{OEBA}$ to A	0.8	3.8	1.0	4.9	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time $\overline{OEAB}$ to B	0.8	4.3	1.0	5.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time $\overline{OEBA}$ to A	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_{PLZ}, t_{PHZ}	Output Disable Time $\overline{OEAB}$ to B	0.8	4.3	1.0	4.9	1.5	8.8	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 12)		0.5		0.5		0.75	ns

Note 11: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, B to A	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8 2.5 3.3	0.25 0.6 0.8	V
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, A to B	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8 2.5 3.3	0.15 0.25 0.35	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, B to A	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8 2.5 3.3	−0.25 −0.6 −0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, A to B	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8 2.5 3.3	0.15 −0.25 −0.35	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, B to A	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8 2.5 3.3	1.5 1.9 2.2	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, A to B	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8 2.5 3.3	1.5 2.05 2.65	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	V_{CC} = 1.8V, 2.5V, or 3.3V, V_I = 0V or V_{CC}	6	pF
$C_{I/O}$	Output Capacitance	V_I = 0V, or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10 MHz V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

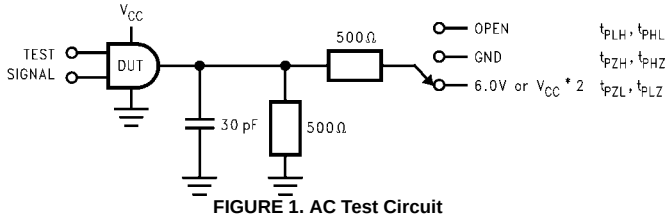


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

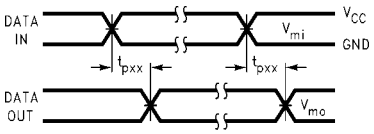


FIGURE 2. Waveform for Inverting and Non-inverting Functions

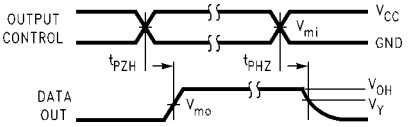


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

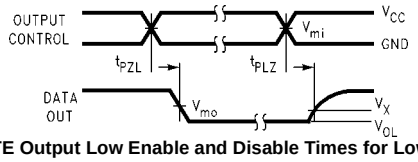


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

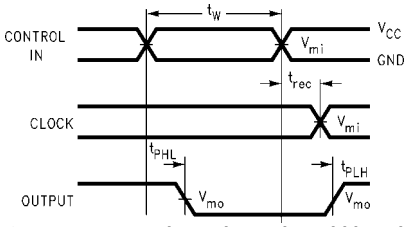


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

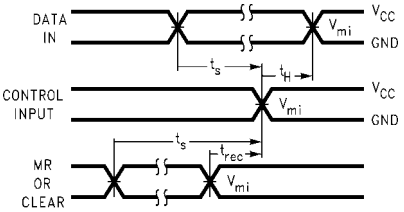
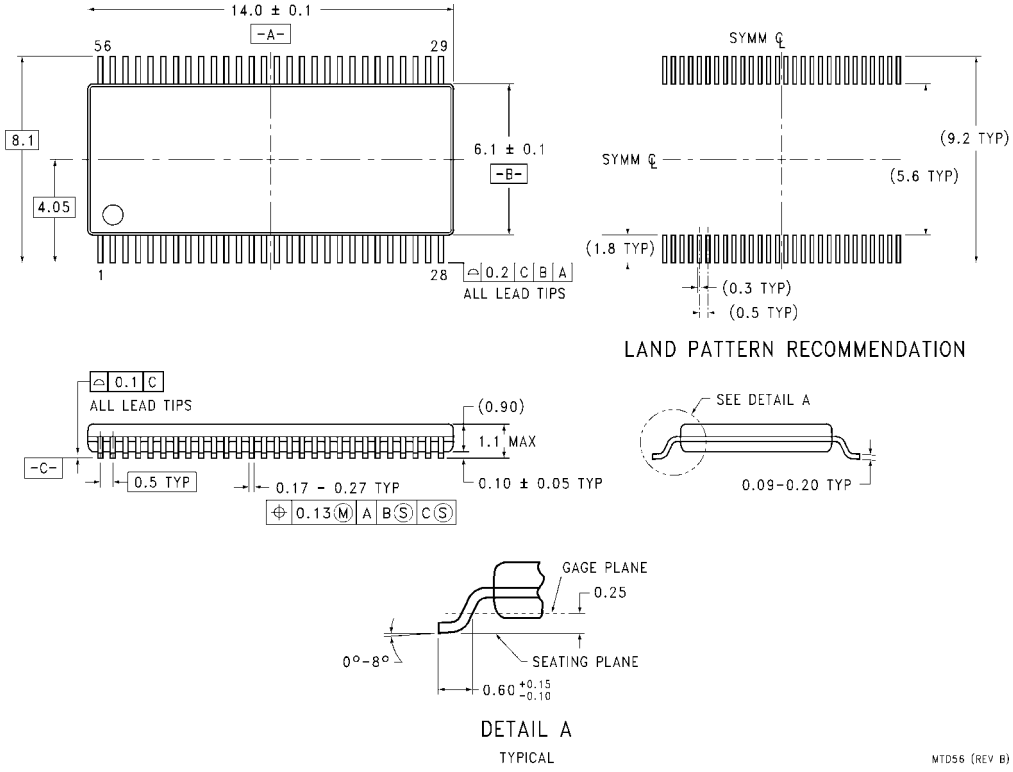


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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March 1998
Revised April 1999

74VCX162827

Low Voltage 20-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in the Outputs

General Description

The VCX162827 contains twenty non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is byte controlled. Each byte has NOR output enables for maximum control flexibility.

The 74VCX162827 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The VCX162827 is also designed with 26Ω resistors in the outputs.

The 74VCX162827 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD}
  - 3.4 ns max for 3.0V to 3.6V V_{CC}
  - 4.1 ns max for 2.3V to 2.7V V_{CC}
  - 8.2 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

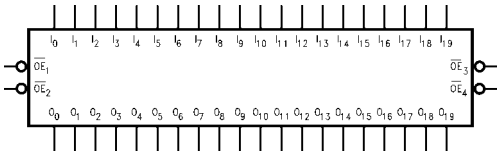
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX162827MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix "X" to the ordering code.

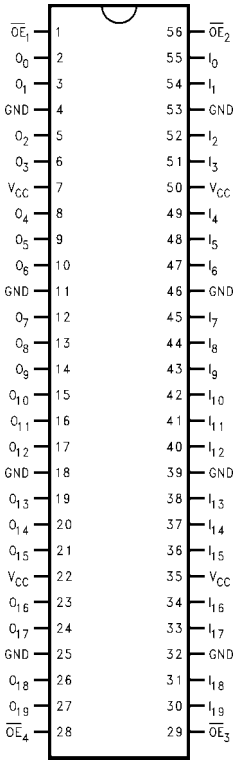
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{19}	Inputs
O_0–O_{19}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_9	O_0–O_9
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

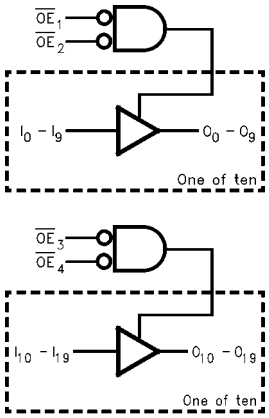
Inputs			Outputs
$\overline{OE}_3$	$\overline{OE}_4$	I_0–I_9	O_{10}–O_{19}
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162827 contains twenty non-inverting buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of each other. The control pins may be shorted together to obtain full 20-bit operation. The 3-STATE outputs are controlled by Output Enable ($\overline{OE}_n$) inputs. When $\overline{OE}_1$, and $\overline{OE}_2$ are LOW, O_0–O_{10} are in the 2-state mode. When either $\overline{OE}_1$ or $\overline{OE}_2$ are HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs. The same applies for byte two with $\overline{OE}_3$ and $\overline{OE}_4$.

Logic Diagrams



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature	
(T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = –4 mA	2.3	2.0		V
		I_{OH} = –6 mA	2.3	1.8		V
		I_{OH} = –8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 6 mA	2.3		0.4	V
		I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = –3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.4	1.0	4.1	1.5	8.2	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	4.3	1.0	5.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.3	1.0	4.9	1.5	8.8	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

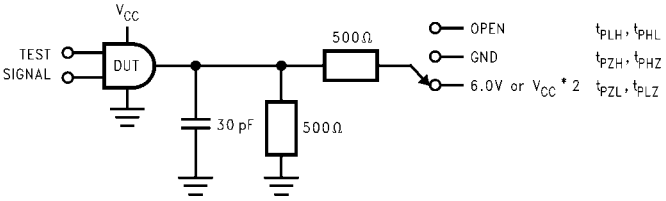
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC}	$T_A = +25°C$	Units
			(V)	Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	
			2.5	–0.25	V
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

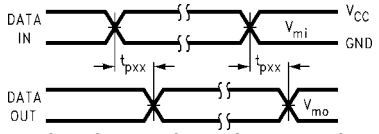


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

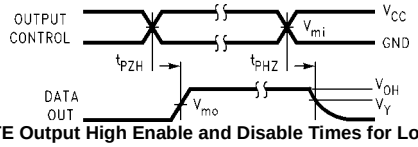


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

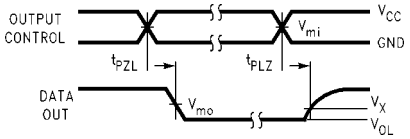
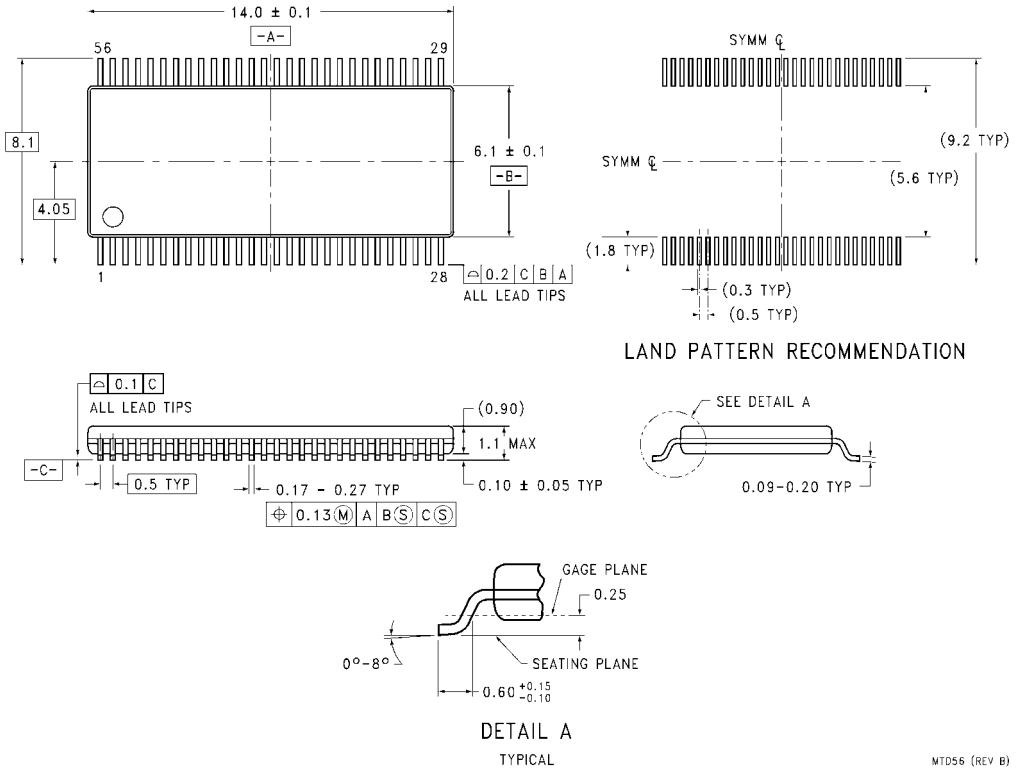


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1998
Revised July 1999

74VCX162835
Low Voltage 18-Bit Universal Bus Driver with 3.6V Tolerant Inputs/Outputs and 26Ω Series Resistors in Outputs

General Description

The VCX162835 low voltage 18-bit universal bus driver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched and clocked modes.

Data flow is controlled by output-enable ($\overline{OE}$), latch-enable (LE), and clock (CLK) inputs. The device operates in Transparent Mode when LE is held HIGH. The device operates in clocked mode when LE is LOW and CLK is toggled. Data transfers from the Inputs (I_n) to Outputs (O_n) on a Positive Edge Transition of the Clock. When $\overline{OE}$ is LOW, the output data is enabled. When $\overline{OE}$ is HIGH the output port is in a high impedance state.

The VCX162835 is designed with 26Ω series resistors in the outputs. This design reduces noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162835 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX162835 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 DIMM module specifications
- 1.65V–3.6V V_{CC} specifications provided
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD} (CP to O_n)
  - 4.2ns max for 3.0V to 3.6V V_{CC}
  - 5.2ns max for 2.3V to 2.7V V_{CC}
  - 9.2ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

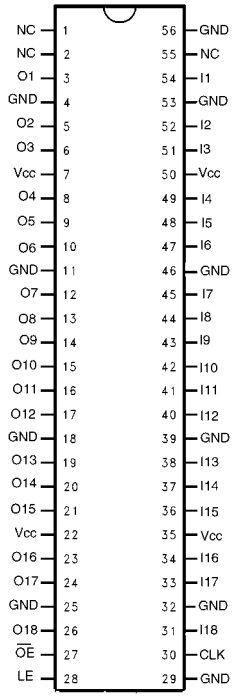
Note 1: To ensure the high impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pulldown resistor; the minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX162835MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable Input
CP	Clock Input
I_1 - I_{18}	Data Inputs
O_1 - O_{18}	3-STATE Outputs

Function Table

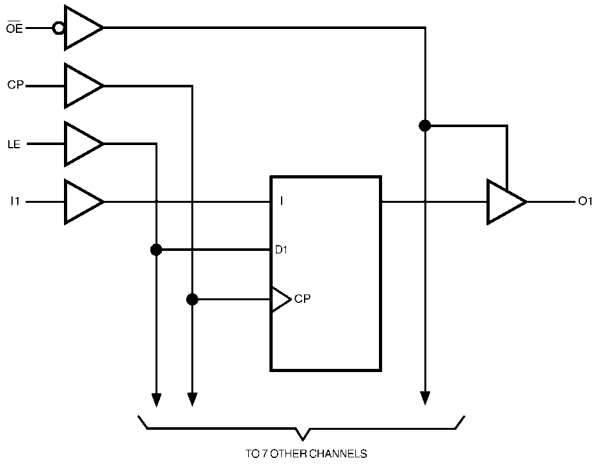
Inputs				Outputs
$\overline{OE}$	LE	CP	I_n	O_n
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	↑	L	L
L	L	↑	H	H
L	L	H	X	Io (Note 2)
L	L	L	X	Io (Note 3)

H = HIGH Voltage Level
L = LOW Level Voltage
X = Immaterial (HIGH or LOW, Inputs may not float)
Z = High Impedance

Note 2: Output level before the indicated steady-state input conditions were established provided that CP was HIGH before LE went LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Logic Diagram



Absolute Maximum Ratings (Note 4)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 5)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 6)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 4: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		
		I_{OH} = −8 mA	3.0	2.4		
		I_{OH} = −12 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 6mA	2.7		0.4	
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12mA	3.0		0.8	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 7)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ μA	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	2.3	2.0		
		$I_{OH} = -6$ mA	2.3	1.8		
		$I_{OH} = -8$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ μA	2.3–2.7		0.2	V
		$I_{OL} = 6$ mA	2.3		0.4	
		$I_{OL} = 8$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 8)	2.3–2.7		±20	

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ μA	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ μA	1.65 - 2.3		0.2	V
		$I_{OL} = 3$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 9)	1.65 - 2.3		±20	

Note 9: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Propagation Delay Bus to Bus	0.6	3.9	0.8	5.0	1.5	9.8	ns
t_{PHL}, t_{PLH}	Propagation Delay Clock to Bus	1.4	4.2	1.5	5.2	2.0	9.2	ns
t_{PHL}, t_{PLH}	Propagation Delay LE to Bus	0.6	4.7	0.8	5.8	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.6	4.3	0.8	5.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.6	4.2	0.8	4.7	1.5	7.9	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 11)		0.5		0.5		0.75	ns

Note 10: For CL=50pF, add approximately 300ps to the AC maximum specification.

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

AC Electrical Characteristics Over Load (Note 12)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.15V$				Units
		$C_L = 0$ pF		$C_L = 50$ pF		
		Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay Bus to Bus	0.7	2.6	1.0	4.2	ns
t_{PHL}, t_{PLH}	Prop Delay Clock to Bus	1.4	2.9	1.9	4.5	ns
t_{PHL}, t_{PLH}	Prop Delay LE to Bus	0.7	3.4	1.0	5.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.7	3.0	1.0	4.6	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.7	2.9	1.0	4.5	ns
t_{PHL}, t_{PLH}	SSO Prop Delay Clock to Bus (Note 13)	1.4	3.2			ns
t_S	Setup Time	1.5		1.5		ns
t_H	Hold Time	0.7		0.7		ns

Note 12: Characterized only.

Note 13: SSO=Simultaneous Switching Output. Any output combination of LOW-to-HIGH and/or HIGH-to-LOW transition.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.35	
			3.3	0.45	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.25	V
			2.5	−0.35	
			3.3	−0.45	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.35	V
			2.5	1.85	
			3.3	2.45	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V, or 3.3V,	3.5	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	5.5	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	13	pF

I_{OUT} - V_{OUT} Characteristics

I_{OH} versus V_{OH}

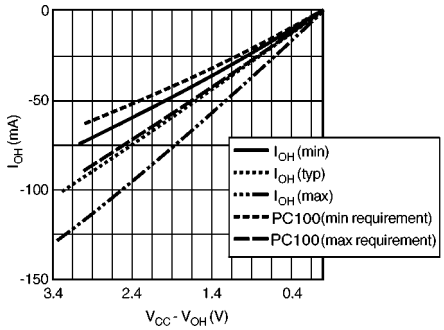


FIGURE 1. Characteristics for Output - Pull Up Drive

I_{OL} versus V_{OL}

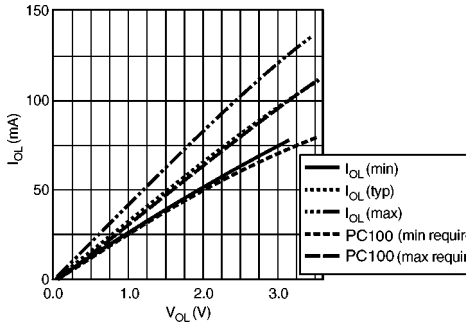


FIGURE 2. Characteristics for Output - Pull Down Driver

AC Loading and Waveforms

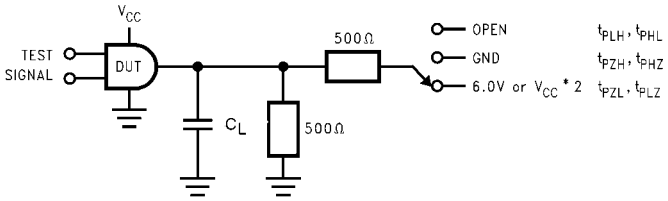


FIGURE 3. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V to ± 0.15V
t_{PZH}, t_{PHZ}	GND

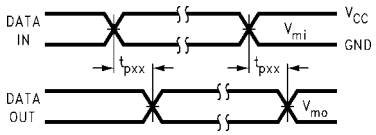


FIGURE 4. Waveform for Inverting and Non-inverting Functions
$t_r = t_f \leq$ 2.0ns, 10% to 90%

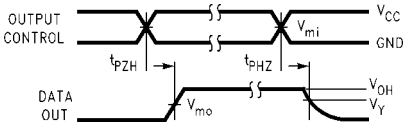


FIGURE 5. 3-STATE Output High Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

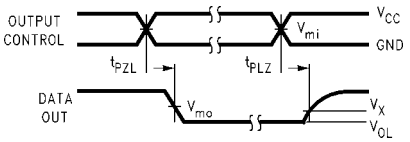
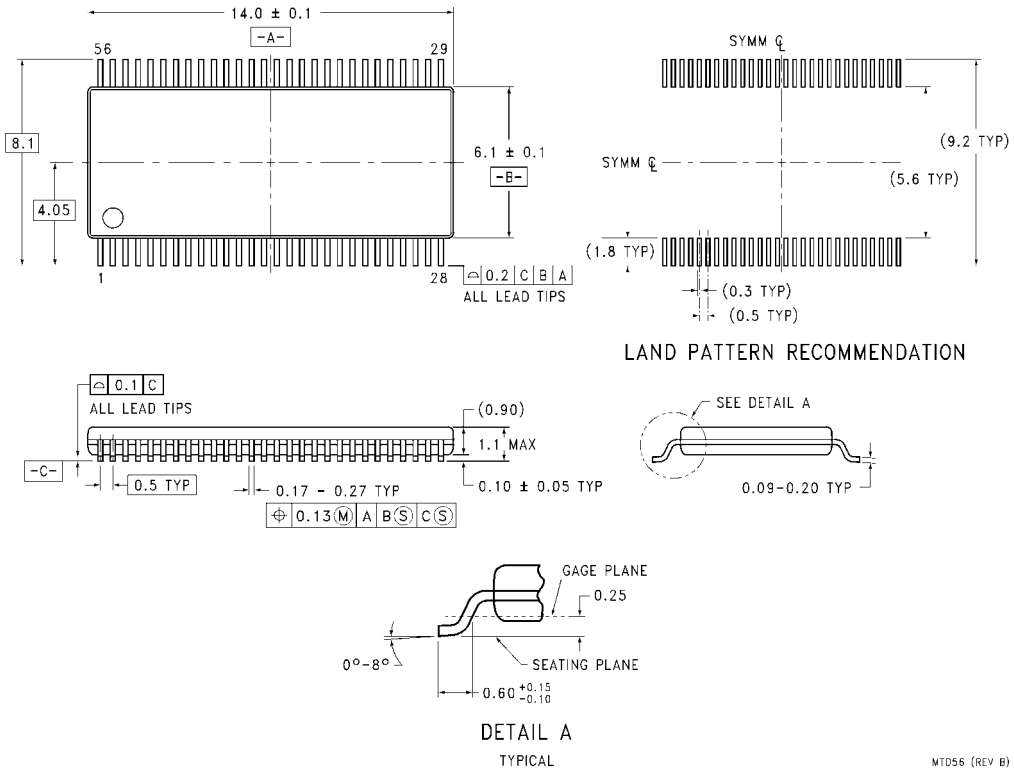


FIGURE 6. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8 ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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August 1997
Revised April 1999

74VCX162838

Low Voltage 16-Bit Selectable Register/Buffer with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in the Outputs

General Description

The VCX162838 contains sixteen non-inverting selectable buffered or registered paths. The device can be configured to operate in a registered, or flow through buffer mode by utilizing the register enable (REGE) and Clock (CP) signals. The device operates in a 16-bit word wide mode. All outputs can be placed into 3-State through the use of the $\overline{OE}$ pin. These devices are ideally suited for buffered or registered 168 pin and 200 pin SDRAM DIMM memory modules.

The 74VCX162838 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V. The VCX162838 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162838 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 and PC133 DIMM module specifications
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in the outputs
- t_{PD} (CP to O_n)
  - 3.9 ns max for 3.0V to 3.6V V_{CC}
  - 5.4 ns max for 2.3V to 2.7V V_{CC}
  - 9.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

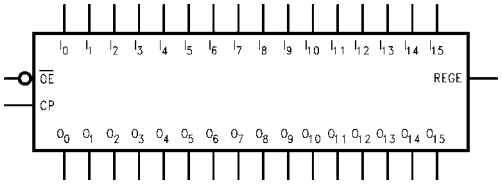
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor. The minimum value of the resistor is determined by the current -sourcing capability of the driver.

Ordering Code:

Ordering Code	Package Number	Package Descriptions
74VCX162838MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

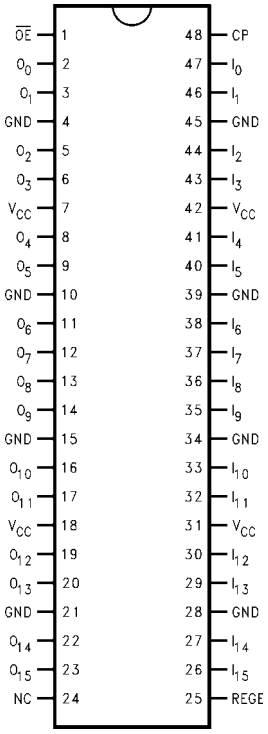
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs
CP	Clock Pulse Input
REGE	Register Enable Input

Connection Diagram



Truth Table

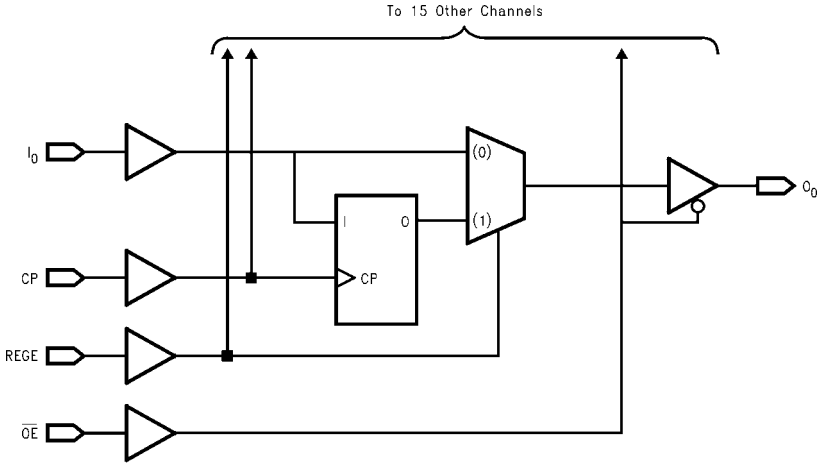
Inputs				Outputs
CP	**REGE**	**I_n**	**$\overline{OE}$**	**O_n**
↑	H	H	L	H
↑	H	L	L	L
X	L	H	L	H
X	L	L	L	L
X	X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162838 consists of sixteen selectable non-inverting buffers or registers with word wide controls. Mode functionality is selected through operation of the CP and REGE pin as shown by the truth table. When REGE is held at a logic "1" the device operates as a 16-bit register. Data is transferred from I_n to O_n on the rising edge of the CP pin. When the REGE pin is held at a logic "0" the device operates in a flow through mode and data propagates directly from the I to the O outputs. All outputs can be 3-stated by holding the $\overline{OE}$ pin at a logic "1".

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -4$ mA	2.3	2.0		V
		$I_{OH} = -6$ mA	2.3	1.8		V
		$I_{OH} = -8$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	2.3–2.7		0.2	V
		$I_{OL} = 6$ mA	2.3		0.4	V
		$I_{OL} = 8$ mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3–2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	1.65 - 2.3		0.2	V
		$I_{OL} = 3$ mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	0.8	3.5	1.0	4.9	1.5	9.8	ns
t_{PHL}, t_{PLH}	Prop Delay CP to O_n (REGE = 1)	0.8	3.9	1.0	5.4	1.5	9.8	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	0.8	3.9	1.0	5.4	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	4.0	1.0	5.7	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.1	1.0	4.6	1.5	8.3	ns
t_S	Setup Time	1.0		1.0		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Extended AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.3V$		Units
		$C_L = 50$ pF		
		Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	1.0	3.8	ns
t_{PHL}, t_{PLH}	Prop Delay CP to O_n (REGE = 1)	1.4	4.2	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	1.0	4.2	ns
t_{PZL}, t_{PZH}	Output Enable Time	1.0	4.3	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	1.0	4.4	ns
t_S	Setup Time	1.0		ns
t_H	Hold Time	0.7		ns

Note 10: This parameter is guaranteed by characterization but not tested.

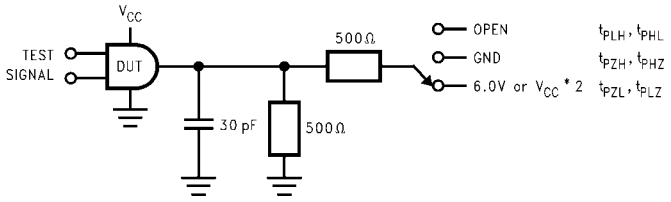
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	V
			2.5	0.25	
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	V
			2.5	–0.25	
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	V
			2.5	2.05	
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

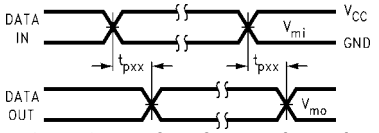


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

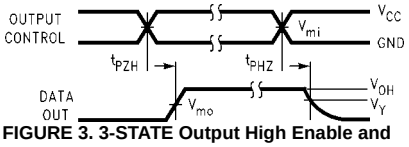


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

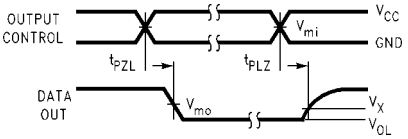


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

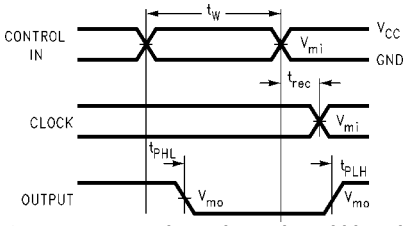


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

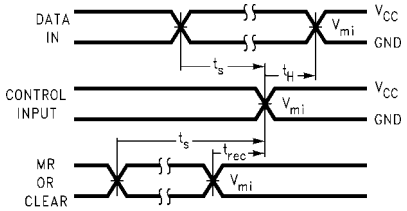
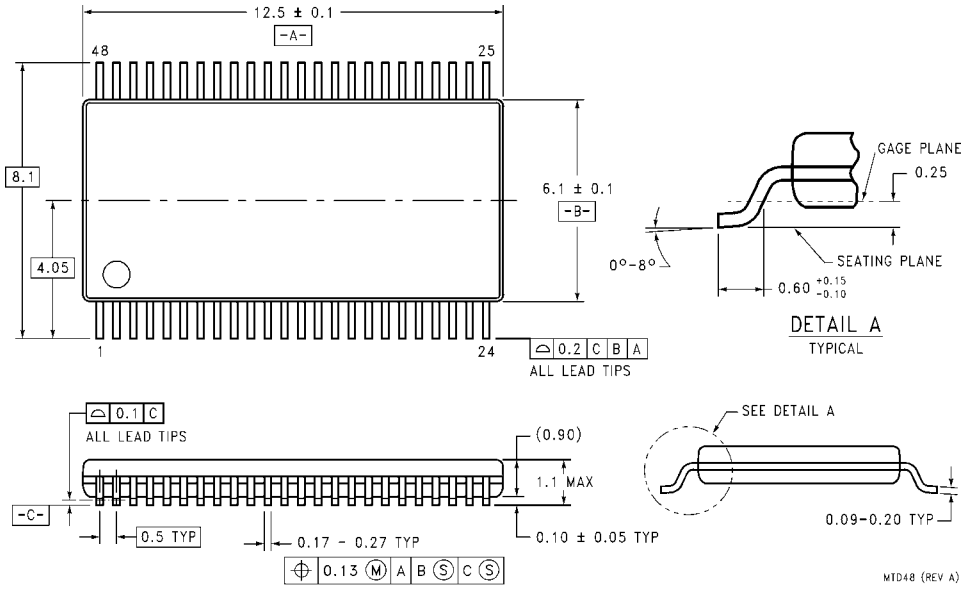


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

March 1998
Revised July 1999

74VCX162839

Low Voltage 20-Bit Selectable Register/Buffer with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in the Outputs

General Description

The VCX162839 contains twenty non-inverting selectable buffered or registered paths. The device can be configured to operate in a registered, or flow through buffer mode by utilizing the register enable (REGE) and Clock (CP) signals. The device operates in a 20-bit word wide mode. All outputs can be placed into 3-STATE through use of the $\overline{OE}$ pin. These devices are ideally suited for buffered or registered 168 pin and 200 pin SDRAM DIMM memory modules.

The 74VCX162839 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V. The 74VCX162839 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162839 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 and PC133 DIMM module specifications
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in the outputs
- t_{PD} (CP to O_n)
  - 4.1 ns max for 3.0V to 3.6V V_{CC}
  - 5.8 ns max for 2.3V to 2.7V V_{CC}
  - 9.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

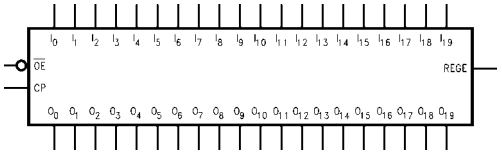
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX162839MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

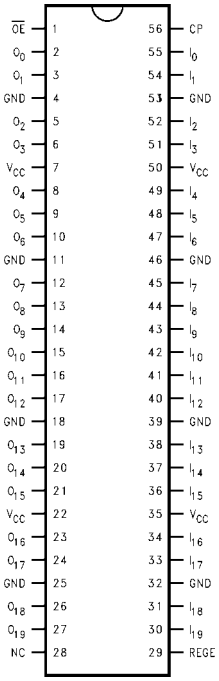
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
I_0–I_{19}	Inputs
O_0–O_{19}	Outputs
CP	Clock Pulse Input
REGE	Register Enable Input

Connection Diagram



Truth Table

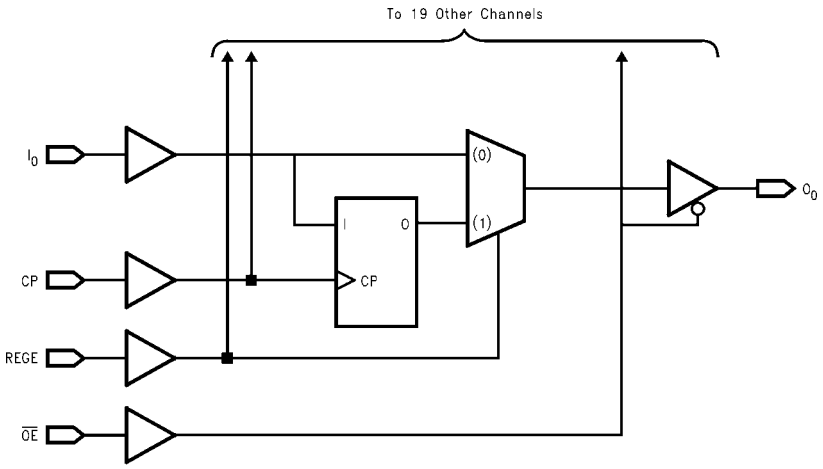
Inputs				Outputs
CP	REGE	I_n	$\overline{OE}$	O_n
↑	H	H	L	H
↑	H	L	L	L
X	L	H	L	H
X	L	L	L	L
X	X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162839 consists of twenty selectable non-inverting buffers or registers with word wide controls. Mode functionality is selected through operation of the CP and REGE pin as shown by the truth table. When REGE is held at a logic "1" the device operates as a 20-bit register. Data is transferred from I_n to O_n on the rising edge of the CP pin. When the REGE pin is held at a logic "0" the device operates in a flow through mode and data propagates directly from the I_n to the O_n outputs. All outputs can be 3-stated by holding the $\overline{OE}$ pin at a logic "1."

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −6 mA	2.7	2.2		V
		I_{OH} = −8 mA	3.0	2.4		V
		I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	V
		I_{OL} = 8 mA	3.0		0.55	V
		I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = −4 mA	2.3	2.0		V
		I_{OH} = −6 mA	2.3	1.8		V
		I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 6 mA	2.3		0.4	V
		I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	0.65 x V_{CC}		
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		0.35 × V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		125		MHz
t_{PHL} t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	0.8	3.5	1.0	4.9	1.5	9.8	ns
t_{PHL} t_{PLH}	Prop Delay CP to O_n (REGE = 1)	0.8	4.1	1.0	5.8	1.5	9.8	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	0.8	4.9	1.0	6.4	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	4.3	1.0	6.1	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.3	1.0	4.9	1.5	8.8	ns
t_S	Setup Time	1.0		1.0		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{osHL} t_{osLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Extended AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.3V$		Units
		$C_L = 50$ pF		
		Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	1.0	3.8	ns
t_{PHL}, t_{PLH}	Prop Delay CP to O_n (REGE = 1)	1.4	4.4	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	1.0	5.2	ns
t_{PZL}, t_{PZH}	Output Enable Time	1.0	4.6	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	1.0	4.6	ns
t_S	Setup Time	1.0		ns
t_H	Hold Time	0.7		ns

Note 10: This parameter is guaranteed by characterization but not tested.

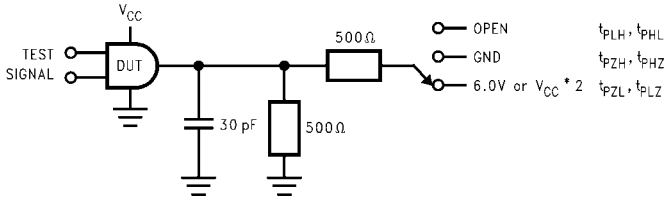
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	V
			2.5	0.25	
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	V
			2.5	–0.25	
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	V
			2.5	2.05	
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

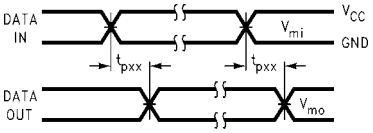


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

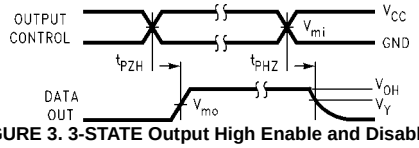


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

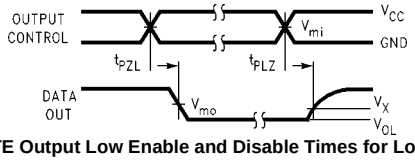


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

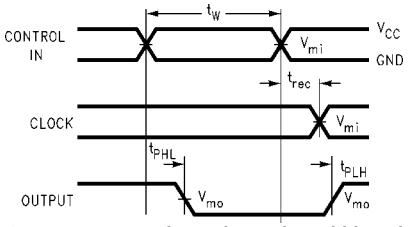


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

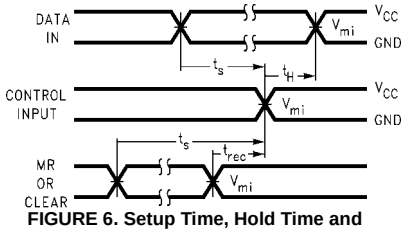
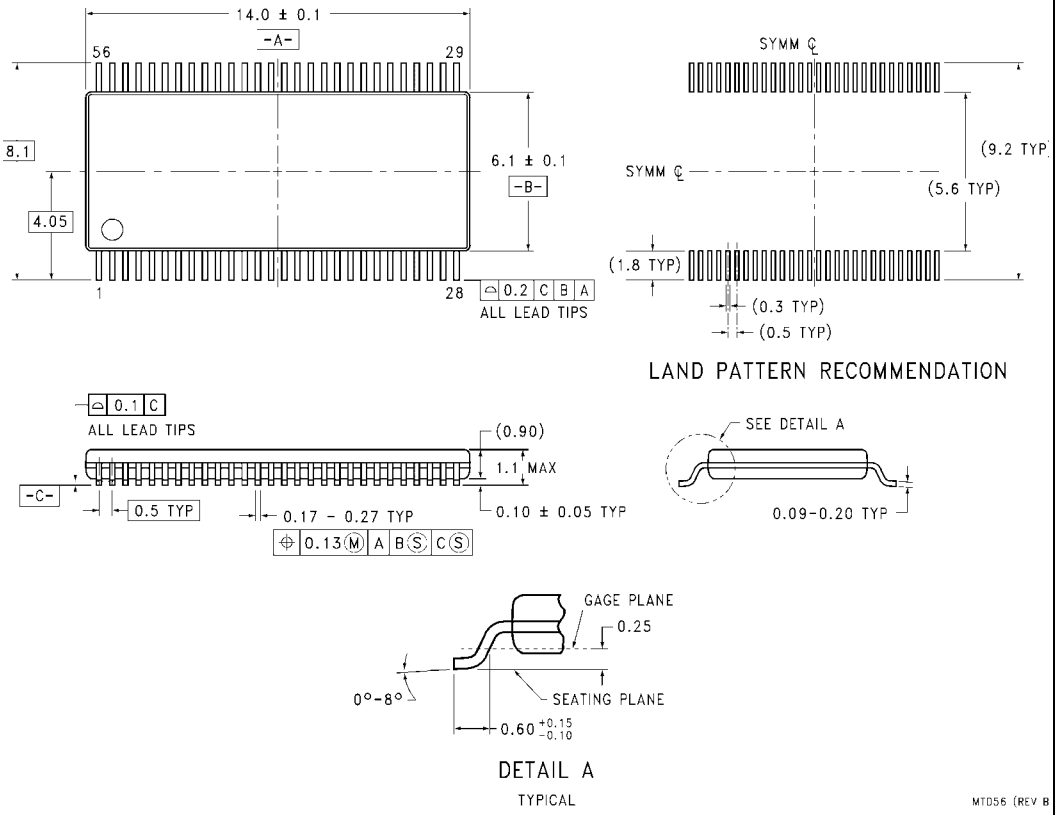


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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FAIRCHILD SEMICONDUCTOR™

December 1999
Revised December 1999

74VCX163245

Low Voltage 16-Bit Dual Supply Translating Transceiver with 3-STATE Outputs (Preliminary)

General Description

The VCX163245 is a dual supply, 16-bit translating transceiver that is designed for 2 way asynchronous communication between busses at different supply voltages by providing true signal translation. The supply rails consist of V_{CCA}, which is a higher potential rail operating at 2.3 to 3.6V and V_{CCB}, which is the lower potential rail operating at 1.65 to 2.7V. (V_{CCB} must be less than or equal to V_{CCA} for proper device operation). This dual supply design allows for translation from 1.8V to 2.5V busses to busses at a higher potential, up to 3.3V.

The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports. The Output Enable ($\overline{OE}$) input, when HIGH, disables both A and B Ports by placing them in a High-Z condition. The A Port interfaces with the higher voltage bus (2.7 – 3.3V); The B Port interfaces with the lower voltage bus (1.8 – 2.5V). Also the VCX163245 is designed so that the control pins ($T/\overline{R}_n$, $\overline{OE}_n$) are supplied by V_{CCB}.

The 74VCX163245 is suitable for mixed voltage applications such as notebook computers using a 1.8V CPU and 3.3V peripheral components. It is fabricated with an Advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Bidirectional interface between busses ranging from 1.65V to 3.6V
- Supports Live Insertion and Withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Functionally compatible with 74 series 16245
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human Body Model >2000V
  - Machine model >200V

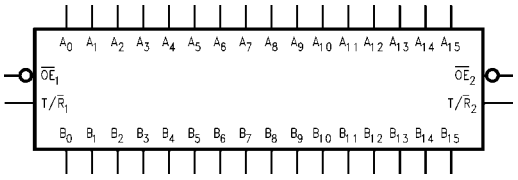
Note 1: To ensure the high impedance state during power up or power down, OE_n should be tied to V_{CCB} through a pull up resistor. The minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX163245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

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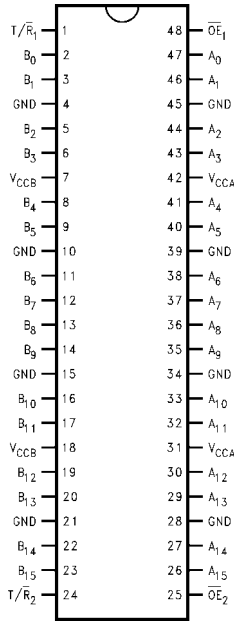
Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

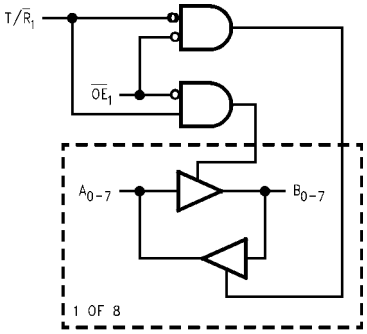
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH-Z State on A_8–A_{15}, B_8–B_{15}

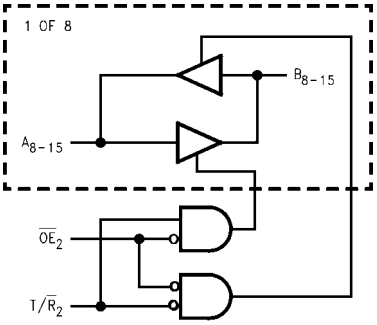
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

VCX163245 Translator Power Up Sequence Recommendations

To guard against power up problems, some simple guidelines need to be adhered to. The VCX163245 is designed so that the control pins ($T/\overline{R}_n$, $\overline{OE}_n$) are supplied by V_{CCB}. Therefore the first recommendation is to begin by powering up the control side of the device, V_{CCB}. The $\overline{OE}_n$ control pins should be ramped with or ahead of V_{CCB}, this will guard against bus contentions and oscillations as all A Port and B Port outputs will be disabled. To ensure the high impedance state during power up or power down, $\overline{OE}_n$ should be tied to V_{CCB} through a pull up resistor. The minimum value of the resistor is determined by the current sourcing capability of the driver. Second, the $T/\overline{R}_n$ control pins should be placed at logic LOW (0V) level, this will ensure that the B-side bus pins are configured as inputs to help guard against bus contention and oscillations. B-side Data Inputs should be driven to a valid logic level (0V or V_{CCB}), this will prevent excessive current draw and oscillations. V_{CCA} can then be powered up after V_{CCB}, however V_{CCA} must be greater than or equal to V_{CCB} to ensure proper device operation. Upon completion of these steps the device can then be configured for the users desired operation. Following these steps will help to prevent possible damage to the translator device as well as other system components.

Logic Diagrams





Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Supply Voltage	
V_{CCA}	−0.5V to +4.6V
V_{CCB}	−0.5V to V_{CCA}
DC Input Voltage (V_I)	−0.5V to +4.6V
DC Output Voltage ($V_{I/O}$)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	
A_n	−0.5V to V_{CCA} + 0.5V
B_n	−0.5V to V_{CCB} + 0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current	±100 mA
Supply Pin (I_{CC} or Ground)	
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply (Note 5)	
V_{CCA}	2.3V to 3.6V
V_{CCB}	1.65V to 2.7V
Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	0V to V_{CCB}
Input/Output Voltage ($V_{I/O}$)	
A_n	0V to V_{CCA}
B_n	0V to V_{CCB}
Output Current in I_{OH}/I_{OL}	
V_{CCA} = 3.0V to 3.6V	±24 mA
V_{CCA} = 2.3V to 2.7V	±18 mA
V_{CCB} = 2.3V to 2.7V	±18 mA
V_{CCB} = 1.65V to 1.95V	±6 mA
Free Air Operating Temperature (T_A	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

Note 5: Operation requires: $V_{CCB} \le V_{CCA}$

DC Electrical Characteristics ($1.65V < V_{CCB} \le 1.95V$, $2.3V < V_{CCA} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CCB} (V)	V_{CCA} (V)	Min	Max	Units
V_{IHA}	HIGH Level Input Voltage	A_n		1.65–1.95	2.3–2.7	1.6		V
V_{IHB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	2.3–2.7	0.65 x V_{CC}		V
V_{ILA}	LOW Level Input Voltage	A_n		1.65–1.95	2.3–2.7		0.7	V
V_{ILB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	2.3–2.7		0.35 x V_{CC}	V
V_{OHA}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	2.3–2.7	V_{CCA}−0.2		V
			I_{OH} = −18 mA	1.65	2.3–2.7	1.7		
V_{OHB}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	2.3–2.7	V_{CCB}−0.2		V
			I_{OH} = −6 mA	1.65–1.95	2.3	1.25		
V_{OLA}	Low Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	2.3–2.7		0.2	V
			I_{OL} = 18 mA	1.65	2.3–2.7		0.6	
V_{OLB}	Low Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	2.3–2.7		0.2	V
			I_{OL} = 6 mA	1.65–1.95	2.3		0.3	
I_I	Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		0V ≤ V_I ≤ 3.6V	1.65–1.95	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage		0V ≤ V_O ≤ 3.6V $\overline{OE}$ = V_{CCB} V_I = V_{IH} or V_{IL}	1.65–1.95	2.3–2.7		±10	µA
I_{OFF}	Power Off Leakage Current		0≤ (V_I, V_O) ≤ 3.6V	0	0		10	µA
I_{CCA}/I_{CCB}	Quiescent Supply Current, per supply, V_{CCA} / V_{CCB}		A_n = V_{CCA} or GND B_n, $\overline{OE}$, & T/$\overline{R}$ = V_{CCB} or GND	1.65–1.95	2.3–2.7		20	µA
			V_{CCA} ≤ An ≤ 3.6V V_{CCB} ≤ B_n, $\overline{OE}$, T/$\overline{R}$ ≤ 3.6V	1.65–1.95	2.3–2.7		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input, B_n, T/$\overline{R}$, $\overline{OE}$		V_I = V_{CCB} − 0.6V	1.65–1.95	2.3–2.7		750	µA
	Increase in I_{CC} per Input, A_n		V_I = V_{CCA} − 0.6V	1.65–1.95	2.3–2.7		750	µA

DC Electrical Characteristics ($1.65V < V_{CCB} \leq 1.95V$, $3.0V < V_{CCA} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CCB} (V)	V_{CCA} (V)	Min	Max	Units
V_{IHA}	HIGH Level Input Voltage	A_n		1.65–1.95	3.0–3.6	2.0		V
V_{IHB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	3.0–3.6	0.65 x V_{CC}		V
V_{ILA}	LOW Level Input Voltage	A_n		1.65–1.95	3.0–3.6		0.8	V
V_{ILB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	3.0–3.6		0.35 x V_{CC}	V
V_{OHA}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	3.0–3.6	V_{CCA}–0.2		V
			I_{OH} = −24 mA	1.65	3.0–3.6	2.2		
V_{OHB}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	3.0–3.6	V_{CCA}–0.2		V
			I_{OH} = −6 mA	1.65–1.95	3.0	1.25		
V_{OLA}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	3.0–3.6		0.2	V
			I_{OL} = 24 mA	1.65	3.0–3.6		0.55	
V_{OLB}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	3.0–3.6		0.2	V
			I_{OL} = 6 mA	1.65–1.95	3.0		0.3	
I_I	Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		0V ≤ V_I ≤ 3.6V	1.65–1.95	3.0–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage		0V ≤ V_O ≤ 3.6V OE* = V_{CCB} V_I = V_{IH} or V_{IL}	1.65–1.95	3.0–3.6		±10	µA
I_{OFF}	Power OFF Leakage Current		0 ≤ (V_I, V_O) ≤ 3.6V	0	0		10	µA
I_{CCA}/I_{CCB}	Quiescent Supply Current, per supply, V_{CCA}/V_{CCB}		A_n = V_{CCA} or GND B_n, $\overline{OE}$, & T/$\overline{R}$ = V_{CCB} or GND	1.65–1.95	3.0–3.6		20	µA
			V_{CCA} ≤ A_n ≤ 3.6V V_{CCB} ≤ B_n, $\overline{OE}$, T/$\overline{R}$ ≤ 3.6V	1.65–1.95	3.0–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input, B_n, T/$\overline{R}$, $\overline{OE}$		V_I = V_{CCB} − 0.6V	1.65–1.95	3.0–3.6		750	µA
	Increase in I_{CC} per Input, A_n		V_I = V_{CCA} − 0.6V	1.65–1.95	3.0–3.6		750	µA

DC Electrical Characteristics ($2.3V < V_{CCB} \leq 2.7V$, $3.0V \leq V_{CCA} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CCB} (V)	V_{CCA} (V)	Min	Max	Units
V_{IHA}	HIGH Level Input Voltage	A_n		2.3–2.7	3.0–3.6	2.0		V
V_{IHB}		B_n, T/$\overline{R}$, $\overline{OE}$		2.3–2.7	3.0–3.6	1.6		V
V_{ILA}	LOW Level Input Voltage	A_n		2.3–2.7	3.0–3.6		0.8	V
V_{ILB}		B_n, T/$\overline{R}$, $\overline{OE}$		2.3–2.7	3.0–3.6		0.7	V
V_{OHA}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.3–2.7	3.0–3.6	V_{CCA}–0.2		V
			I_{OH} = −24 mA	2.3	3.0–3.6	2.2		
V_{OHB}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.3–2.7	3.0–3.6	V_{CCB}–0.2		V
			I_{OH} = −18 mA	2.3–2.7	3.0	1.7		
V_{OLA}	LOW Level Output Voltage		I_{OL} = 100 µA	2.3–2.7	3.0–3.6		0.2	V
			I_{OL} = 24 mA	2.3	3.0–3.6		0.55	
V_{OLB}	LOW Level Output Voltage		I_{OL} = 100 µA	2.3–2.7	3.0–3.6		0.2	V
			I_{OL} = 18 mA	2.3–2.7	3.0		0.6	
I_I	Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		0V ≤ V_I ≤ 3.6V	2.3–2.7	3.0–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage @ A_n		0V ≤ V_O ≤ 3.6V $\overline{OE}$ = V_{CCA} V_I = V_{IH} or V_{IL}	2.3–2.7	3.0–3.6		±10	µA
I_{OFF}	Power OFF Leakage Current		0 ≤ (V_I, V_O) ≤ 3.6V	0	0		10	µA
I_{CCA}/I_{CCB}	Quiescent Supply Current, per supply, V_{CCA}/V_{CCB}		A_n = V_{CCA} or GND B_n, $\overline{OE}$, & T/$\overline{R}$ = V_{CCB} or GND	2.3–2.7	3.0–3.6		20	µA
			V_{CCA} ≤ A_n ≤ 3.6V V_{CCB} ≤ B_n, $\overline{OE}$, T/$\overline{R}$ ≤ 3.6V	2.3–2.7	3.0–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input, B_n, T/$\overline{R}$, $\overline{OE}$		V_I = V_{CCB} − 0.6V	2.3–2.7	3.0–3.6		750	µA
	Increase in I_{CC} per Input, A_n		V_I = V_{CCA} − 0.6V	2.3–2.7	3.0–3.6		750	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		V_{CCB} = 1.65V to 1.95V V_{CCA} = 2.3V to 2.7V		V_{CCB} = 1.65V to 1.95V V_{CCA} = 3.0V to 3.6V		V_{CCB} = 2.3V to 2.7V V_{CCA} = 3.0V to 3.6V		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay, A to B	1.5	5.8	1.5	6.2	0.8	4.4	ns
t_{PHL}, t_{PLH}	Prop Delay, B to A	0.8	5.5	0.6	5.1	0.6	4.0	ns
t_{PZL}, t_{PZH}	Output Enable Time, OE to B	1.5	8.3	1.5	8.2	0.8	4.6	ns
t_{PZL}, t_{PZH}	Output Enable Time, OE to A	0.8	5.3	0.6	5.1	0.6	4.0	ns
t_{PLZ}, t_{PHZ}	Output Disable Time, OE to B	0.8	4.6	0.8	4.5	0.8	4.4	ns
t_{PLZ}, t_{PHZ}	Output Disable Time, OE to A	0.8	5.2	0.6	5.6	0.6	4.8	ns
t_{osHL} t_{osLH}	Output to Output Skew (Note 6)		5.0		0.5		0.75	ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{osHL}) or LOW-to-HIGH (t_{osLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CCB} (V)	V_{CCA} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	2.5	0.25	V
			1.8	3.3	0.25	
			2.5	3.3	0.6	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	2.5	0.6	V
			1.8	3.3	0.8	
			2.5	3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	2.5	–0.25	V
			1.8	3.3	–0.25	
			2.5	3.3	–0.6	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	2.5	–0.6	V
			1.8	3.3	–0.8	
			2.5	3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	2.5	1.5	V
			1.8	3.3	1.5	
			2.5	3.3	1.9	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	2.5	1.9	V
			1.8	3.3	2.2	
			2.5	3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_{CCB} = 2.5V$, $V_{CCA} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	6	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CCB} = 2.5V$, $V_{CCA} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	7	pF
C_{PD}	Power Dissipation Capacitance	$V_{CCB} = 2.5V$, $V_{CCA} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$ f = 10MHz	20	pF

AC Loading and Waveforms

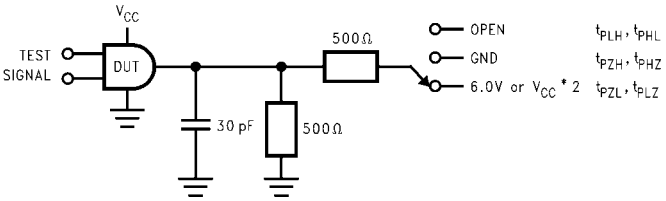


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	OPEN
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ±0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

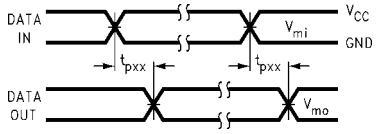


FIGURE 2. Waveform for Inverting and Non-inverting Functions
$t_R = t_F \leq$ 2.0 ns, 10% to 90%

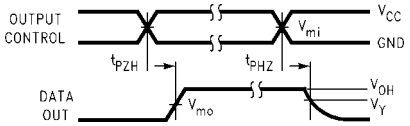


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic
$t_R = t_F \leq$ 2.0 ns, 10% to 90%

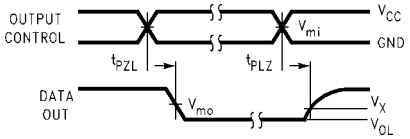
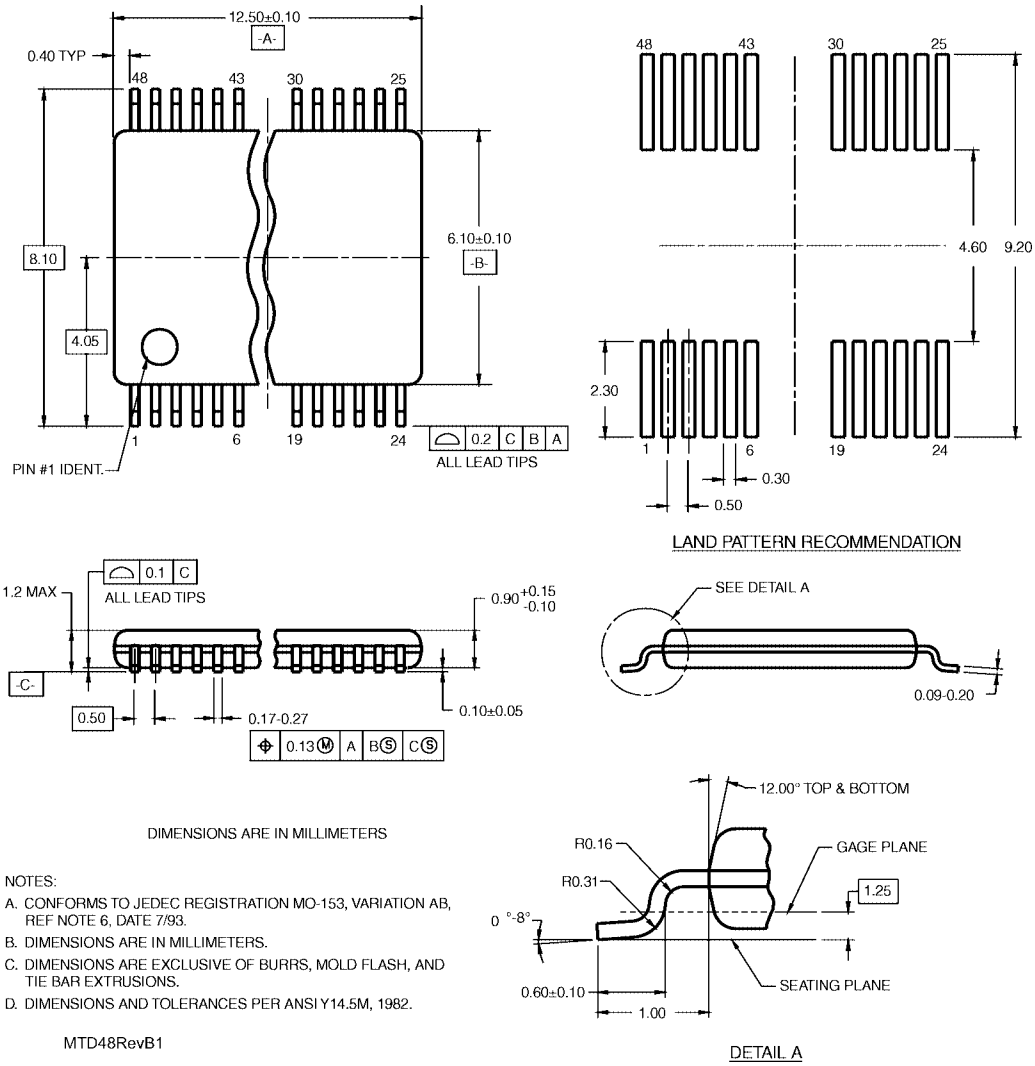


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic
$t_R = t_F \leq$ 2.0 ns, 10% to 90%

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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FAIRCHILD SEMICONDUCTOR™

October 1997
Revised April 1999

74VCX16373
Low Voltage 16-Bit Transparent Latch with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear to be transparent to the data when the Latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The 74VCX16373 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (I_n to O_n)
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 3.4 ns max for 2.3V to 2.7V V_{CC}
  - 6.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Support live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

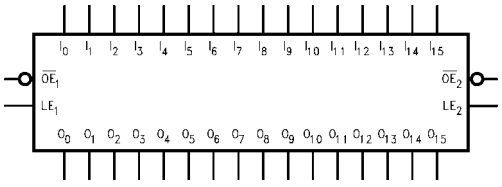
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Ordering Number	Package Number	Package Description
74VCX16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

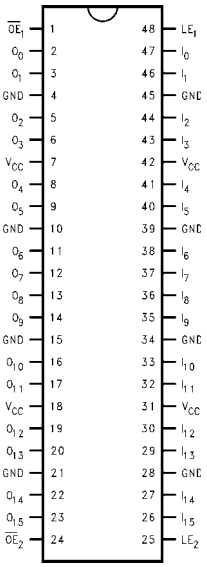
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

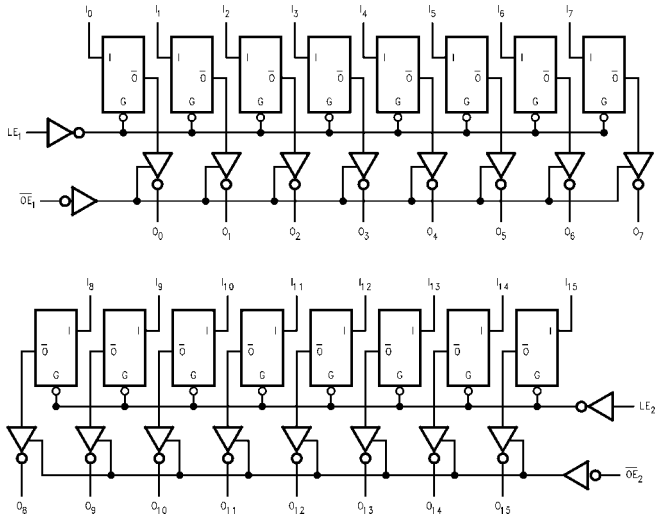
Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCX16373 contains sixteen edge D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition on LE_n. The 3-STATE outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	2.3 – 2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		V
		$I_{OH} = -12$ mA	2.3	1.8		V
		$I_{OH} = -18$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	2.3 – 2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	V
		$I_{OL} = 18$ mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	1.65 - 2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 – 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n	0.8	3.0	1.0	3.4	1.5	6.8	ns
t_{PHL}, t_{PLH}	Prop Delay LE to O_n	0.8	3.0	1.0	3.9	1.5	7.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.6	1.5	9.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

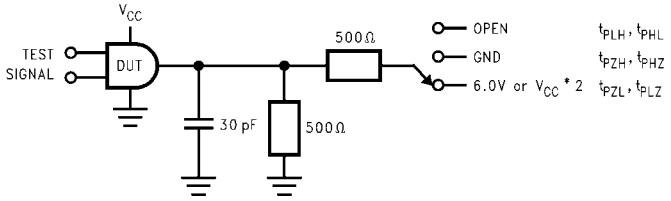
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

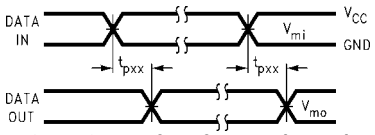


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

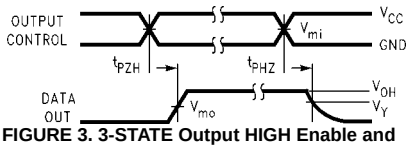


FIGURE 3. 3-STATE Output HIGH Enable and Disable Times for Low Voltage Logic

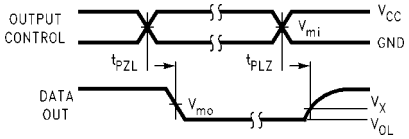


FIGURE 4. 3-STATE Output LOW Enable and Disable Times for Low Voltage Logic

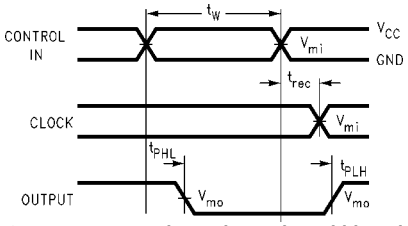


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

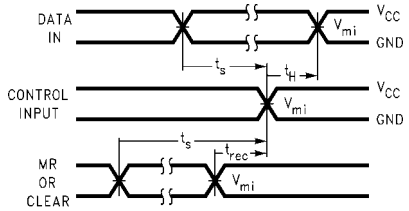
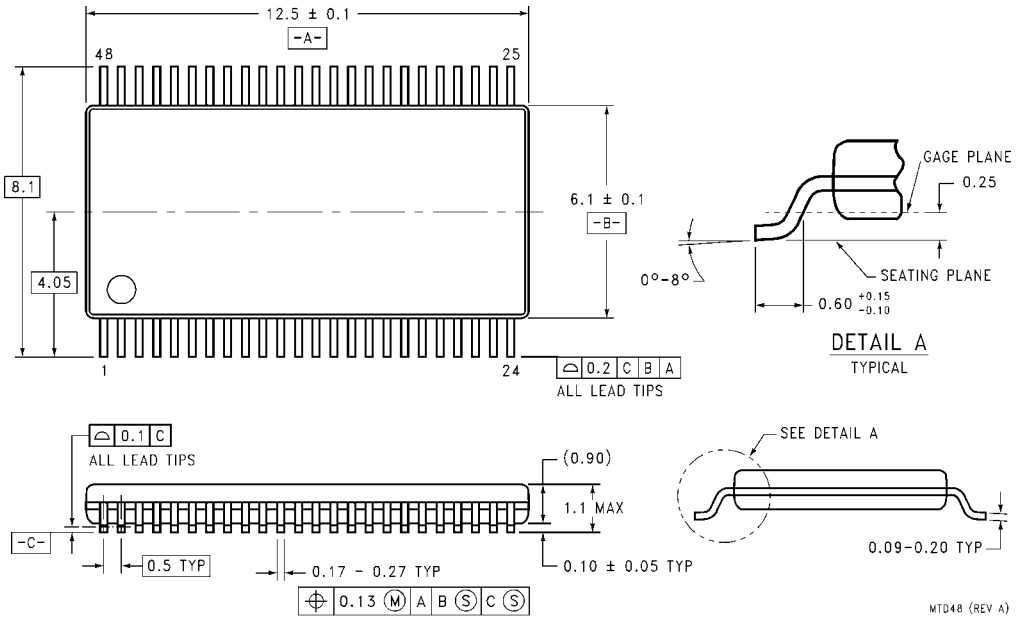


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

October 1997
Revised April 1999

74VCX16374

Low Voltage 16-Bit D-Type Flip-Flop with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and output enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

The 74VCX16374 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 3.9 ns max for 2.3V to 2.7V V_{CC}
  - 7.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

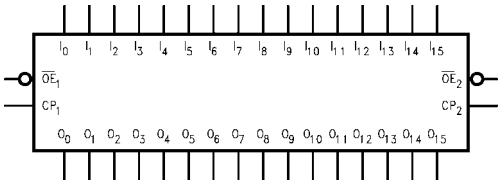
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

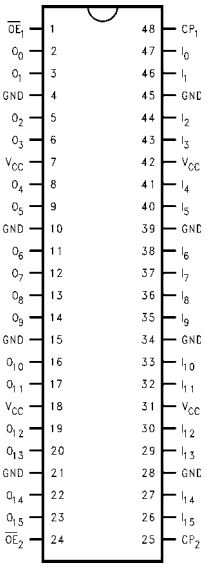
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
↑	L	H	H
↑	L	L	L
L	L	X	O_0
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
↑	L	H	H
↑	L	L	L
L	L	X	O_0
X	H	X	Z

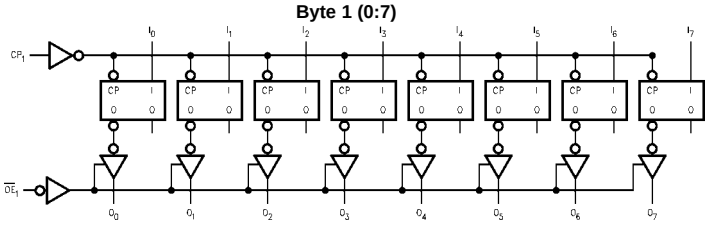
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of CP

Functional Description

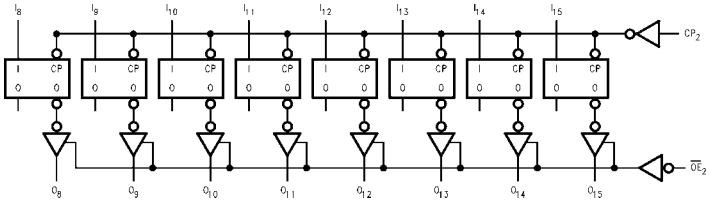
The 74VCX16374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each clock has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual I inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operations of the $\overline{OE}_n$ input does not affect the state of the flip-flops.

Logic Diagram

Byte 1 (0:7)



Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.3	2.0		V
		I_{OH} = −12 mA	2.3	1.8		V
		I_{OH} = −18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} − 0.2		V
		I_{OH} = −6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay CP to O_n	0.8	3.0	1.0	3.9	1.5	7.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.6	1.5	9.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

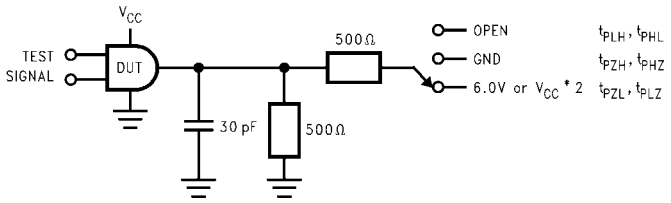
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

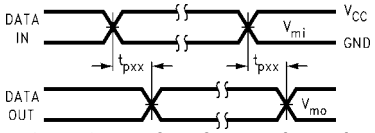


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

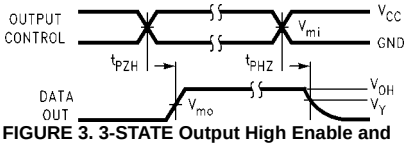


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

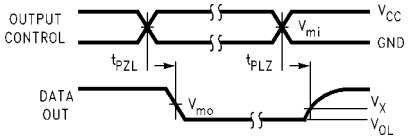


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

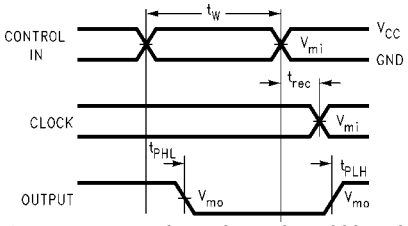


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

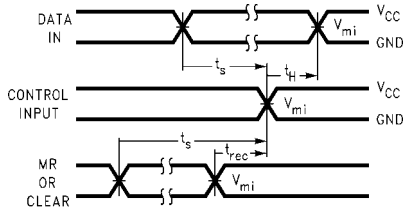
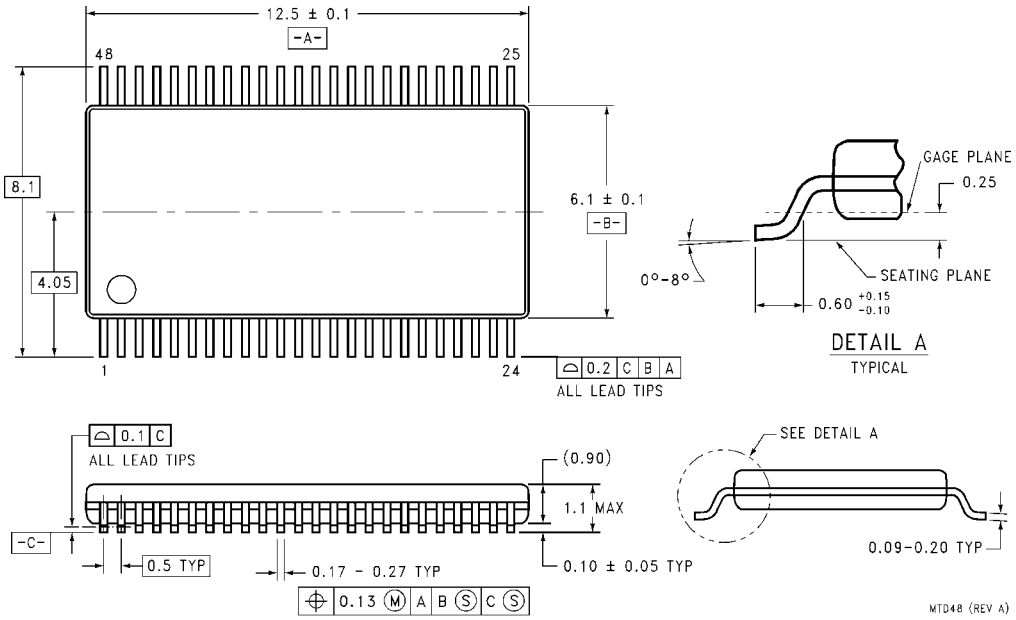


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Body Width
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

December 1999
Revised December 1999

74VCX164245

Low Voltage 16-Bit Dual Supply Translating Transceiver with 3-STATE Outputs (Preliminary)

General Description

The VCX164245 is a dual supply, 16-bit translating transceiver that is designed for 2 way asynchronous communication between busses at different supply voltages by providing true signal translation. The supply rails consist of V_{CCB}, which is the higher potential rail operating at 2.3 to 3.6V and V_{CCA}, which is the lower potential rail operating at 1.65 to 2.7V. (V_{CCA} must be less than or equal to V_{CCB} for proper device operation.) This dual supply design allows for translation from 1.8V to 2.5V busses to busses at a higher potential, up to 3.3V.

The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow. Transmit (active-HIGH) enables data from A Ports to B Ports; Receive (active-LOW) enables data from B Ports to A Ports.The Output Enable ($\overline{OE}$) input, when HIGH, disables both A and P Ports by placing them in a High-Z condition. The A Port interfaces with the lower voltage bus (1.8 – 2.5V); The B Port interfaces with the higher voltage bus (2.7 – 3.3V). Also the VCX164245 is designed so that the control pins ($T/\overline{R}_n$, $\overline{OE}_n$) are supplied by V_{CCB}.

The 74VCX164245 is suitable for mixed voltage applications such as notebook computers using a 1.8V CPU and 3.3V peripheral components. It is fabricated with an Advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Bidirectional interface between busses ranging from 1.65V to 3.6V
- Supports Live Insertion and Withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Functionally compatible with 74 series 16245
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human Body Model >2000V
  - Machine model >200V

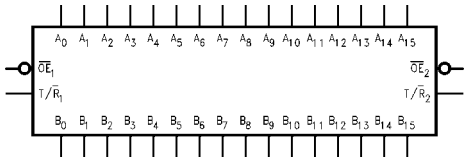
Note 1: To ensure the high impedance state during power up or power down, OE_n should be tied to V_{CCB} through a pull up resistor. The minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX164245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
$T/\overline{R}_n$	Transmit/Receive Input
A_0–A_{15}	Side A Inputs or 3-STATE Outputs
B_0–B_{15}	Side B Inputs or 3-STATE Outputs

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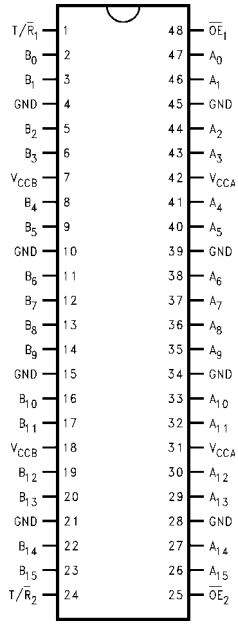
Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	$T/\overline{R}_1$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

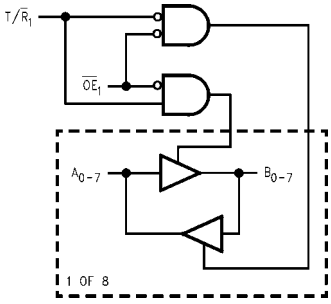
Inputs		Outputs
$\overline{OE}_2$	$T/\overline{R}_2$	
L	L	Bus B_8–B_{15} Data to Bus A_8–A_{15}
L	H	Bus A_8–A_{15} Data to Bus B_8–B_{15}
H	X	HIGH-Z State on A_8–A_{15}, B_8–B_{15}

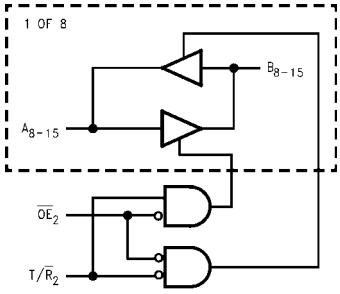
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Translator Power Up Sequence Recommendations

To guard against power up problems, some simple guidelines need to be adhered to. The VCX164245 is designed so that the control pins ($T/\overline{R}n$, $\overline{OE}_n$) are supplied by V_{CCB}. Therefore the first recommendation is to begin by powering up the control side of the device, V_{CCB}. The $\overline{OE}_n$ control pins should be ramped with or ahead of V_{CCB}, this will guard against bus contentions and oscillations as all A-Port and B Port outputs will be disabled. To ensure the high impedance state during power up or power down, $\overline{OE}_n$ should be tied to V_{CCB} through a pull up resistor. The minimum value of the resistor is determined by the current sourcing capability of the driver. Second, the $T/\overline{R}_n$ control pins should be placed at logic low (0V) level, this will ensure that the B-side bus pins are configured as inputs to help guard against bus contention and oscillations. B-side Data Inputs should be driven to a valid logic level (0V or V_{CCB}), this will prevent excessive current draw and oscillations. V_{CCA} can then be powered up after V_{CCB}, but should never exceed the V_{CCB} voltage level. Upon completion of these steps the device can then be configured for the users desired operation. Following these steps will help to prevent possible damage to the translator device as well as other system components.

Logic Diagrams





Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage	
V_{CCA}	−0.5V to V_{CCB}
V_{CCB}	−0.5V to 4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
DC Output Voltage ($V_{I/O}$)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	
An	−0.5V to V_{CCA} + 0.5V
Bn	−0.5V to V_{CCB} + 0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply (Note 5)	
V_{CCA}	1.65V to 2.7V
V_{CCB}	2.3V to 3.6V
Input Voltage (V_I) @ $\overline{OE}$, T/$\overline{R}$	0V to V_{CCB}
Input/Output Voltage ($V_{I/O}$)	
A_n	0V to V_{CCA}
B_n	0V to V_{CCB}
Output Current in I_{OH}/I_{OL}	
V_{CCA} = 2.3V to 2.7V	±18 mA
V_{CCA} = 1.65V to 1.95V	±6 mA
V_{CCB} = 3.0V to 3.6V	±24 mA
V_{CCB} = 2.3V to 2.7V	±18 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

Note 5: Operation requires: $V_{CCA} \le V_{CCB}$

DC Electrical Characteristics ($1.65V < V_{CCA} \le 1.95V$, $2.3V < V_{CCB} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CCA} (V)	V_{CCB} (V)	Min	Max	Units
V_{IHA}	HIGH Level Input Voltage	A_n		1.65–1.95	2.3–2.7	0.65 x V_{CC}		V
V_{IHB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	2.3–2.7	1.6		V
V_{ILA}	LOW Level Input Voltage	A_n		1.6–1.95	2.3–2.7		0.35 x V_{CC}	V
V_{ILB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	2.3–2.7		0.7	V
V_{OHA}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	2.3–2.7	V_{CCA}−0.2		V
			I_{OH} = −6 mA	1.65	2.3–2.7	1.25		
V_{OHB}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	2.3–2.7	V_{CCB}−0.2		V
			I_{OH} = −18 mA	1.65–1.95	2.3	1.7		
V_{OLA}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	2.3–2.7		0.2	V
			I_{OL} = 6 mA	1.65	2.3–2.7		0.3	
V_{OLB}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	2.3–2.7		0.2	V
			I_{OL} = 18 mA	1.65–1.95	2.3		0.6	
I_I	Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		0V ≤ V_I ≤ 3.6V	1.65–1.95	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage		0V ≤ V_O ≤ 3.6V $\overline{OE}$ = V_{CCB} V_I = V_{IH} or V_{IL}	1.65–1.95	2.3–2.7		±10	µA
I_{OFF}	Power OFF Leakage Current		0≤ (V_I, V_O) ≤ 3.6V	0	0		10	µA
I_{CCA}/I_{CCB}	Quiescent Supply Current, per supply, V_{CCA} / V_{CCB}		A_n = V_{CCA} or GND B_n, $\overline{OE}$, & T/$\overline{R}$ = V_{CCB} or GND	1.65–1.95	2.3–2.7		20	µA
			V_{CCA} ≤ A_n ≤ 3.6V V_{CCB} ≤ B_n, $\overline{OE}$, T/$\overline{R}$ ≤ 3.6V	1.65–1.95	2.3–2.7		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input, B_n, T/$\overline{R}$, $\overline{OE}$		V_I = V_{CCB} − 0.6V	1.65–1.95	2.3–2.7		750	µA
	Increase in I_{CC} per Input, A_n		V_I = V_{CCA} − 0.6V	1.65–1.95	2.3–2.7		750	µA

DC Electrical Characteristics ($1.65V < V_{CCA} \leq 1.95V$, $3.0V < V_{CCB} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CCA} (V)	V_{CCB} (V)	Min	Max	Units
V_{IHA}	HIGH Level Input Voltage	A_n		1.65–1.95	3.0–3.6	0.65 x V_{CC}		V
V_{IHB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	3.0–3.6	2.0		V
V_{ILA}	LOW Level Input Voltage	A_n		1.65–1.95	3.0–3.6		0.35 x V_{CC}	V
V_{ILB}		B_n, T/$\overline{R}$, $\overline{OE}$		1.65–1.95	3.0–3.6		0.8	V
V_{OHA}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	3.0–3.6	V_{CCA}–0.2		V
			I_{OH} = −6 mA	1.65	3.0–3.6	1.25		
V_{OHB}	HIGH Level Output Voltage		I_{OH} = −100 µA	1.65–1.95	3.0–3.6	V_{CCA}–0.2		V
			I_{OH} = −24 mA	1.65–1.95	3.0	2.2		
V_{OLA}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	3.0–3.6		0.2	V
			I_{OL} = 6 mA	1.65	3.0–3.6		0.3	
V_{OLB}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65–1.95	3.0–3.6		0.2	V
			I_{OL} = 24 mA	1.65–1.95	3.0		0.55	
I_I	Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		0V ≤ V_I ≤ 3.6V	1.65–1.95	3.0–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage		0V ≤ V_O ≤ 3.6V OE* = V_{CCB} V_I = V_{IH} or V_{IL}	1.65–1.95	3.0–3.6		±10	µA
I_{OFF}	Power Off Leakage Current		0 ≤ (V_I, V_O) ≤ 3.6V	0	0		10	µA
I_{CCA}/I_{CCB}	Quiescent Supply Current, per supply, V_{CCA}/V_{CCB}		A_n = V_{CCA} or GND B_n, $\overline{OE}$, & T/$\overline{R}$ = V_{CCB} or GND	1.65–1.95	3.0–3.6		20	µA
			V_{CCA} ≤ A_n ≤ 3.6V V_{CCB} ≤ B_n, $\overline{OE}$, T/$\overline{R}$ ≤ 3.6V	1.65–1.95	3.0–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input, B_n, T/$\overline{R}$, $\overline{OE}$		V_I = V_{CCB} − 0.6V	1.65–1.95	3.0–3.6		750	µA
	Increase in I_{CC} per Input, A_n		V_I = V_{CCA} − 0.6V	1.65–1.95	3.0–3.6		750	µA

DC Electrical Characteristics ($2.3V < V_{CCA} \leq 2.7V$, $3.0V \leq V_{CCB} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CCA} (V)	V_{CCB} (V)	Min	Max	Units
V_{IHA}	HIGH Level Input Voltage	A_n		2.3–2.7	3.0–3.6	1.6		V
V_{IHB}		B_n, T/$\overline{R}$, $\overline{OE}$		2.3–2.7	3.0–3.6	2.0		V
V_{ILA}	LOW Level Input Voltage	A_n		2.3–2.7	3.0–3.6		0.7	V
V_{ILB}		B_n, T/$\overline{R}$, $\overline{OE}$		2.3–2.7	3.0–3.6		0.8	V
V_{OHA}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.3–2.7	3.0–3.6	V_{CCA}–0.2		V
			I_{OH} = −18 mA	2.3	3.0–3.6	1.7		
V_{OHB}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.3–2.7	3.0–3.6	V_{CCB}–0.2		V
			I_{OH} = −24 mA	2.3–2.7	3.0	2.2		
V_{OLA}	LOW Level Output Voltage		I_{OL} = 100 µA	2.3–2.7	3.0–3.6		0.2	V
			I_{OL} = 18 mA	2.3	3.0–3.6		0.6	
V_{OLB}	LOW Level Output Voltage		I_{OL} = 100 µA	2.3–2.7	3.0–3.6		0.2	V
			I_{OL} = 24 mA	2.3–2.7	3.0		0.55	
I_I	Input Leakage Current @ $\overline{OE}$, T/$\overline{R}$		0V ≤ V_I ≤ 3.6V	2.3–2.7	3.0–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage @ A_n		0V ≤ V_O ≤ 3.6V $\overline{OE}$ = V_{CCA} V_I = V_{IH} or V_{IL}	2.3–2.7	3.0–3.6		±10	µA
I_{OFF}	Power OFF Leakage Current		0 ≤ (V_I, V_O) ≤ 3.6V	0	0		10	µA
I_{CCA}/I_{CCB}	Quiescent Supply Current, per supply, V_{CCA}/V_{CCB}		A_n = V_{CCA} or GND B_n, $\overline{OE}$, & T/$\overline{R}$ = V_{CCB} or GND	2.3–2.7	3.0–3.6		20	µA
			V_{CCA} ≤ A_n ≤ 3.6V V_{CCB} ≤ B_n, $\overline{OE}$, T/$\overline{R}$ ≤ 3.6V	2.3–2.7	3.0–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input, B_n, T/$\overline{R}$, $\overline{OE}$		V_I = V_{CCB} − 0.6V	2.3–2.7	3.0–3.6		750	µA
	Increase in I_{CC} per Input, A_n		V_I = V_{CCA} − 0.6V	2.3–2.7	3.0–3.6		750	µA

AC Electrical Characteristics

Symbol	Parameter	C_L = 30 pF, R_L = 500Ω, T_A = −40°C to +85°C,						Units
		V_{CCA} = 1.65V to 1.95V V_{CCB} = 2.3V to 2.7V		V_{CCA} = 1.65V to 1.95V V_{CCB} = 3.0V to 3.6V		V_{CCA} = 2.3V to 2.7V V_{CCB} = 3.0V to 3.6V		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay, A to B	0.8	5.5	0.6	5.1	0.6	4.0	ns
t_{PHL}, t_{PLH}	Prop Delay, B to A	1.5	5.8	1.5	6.2	0.8	4.4	ns
t_{PZL}, t_{PZH}	Output Enable Time, OE to B	0.8	5.3	0.6	5.1	0.6	4.0	ns
t_{PZL}, t_{PZH}	Output Enable Time, OE to A	1.5	8.3	1.5	8.2	0.8	4.6	ns
t_{PLZ}, t_{PHZ}	Output Disable Time, OE to B	0.8	5.2	0.8	5.6	0.8	4.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time, OE to A	0.8	4.6	0.8	4.5	0.8	4.4	ns
t_{osHL} t_{osLH}	Output to Output Skew (Note 6)		0.5		0.5		0.75	ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{osHL}) or LOW-to-HIGH (t_{osLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CCA} (V)	V_{CCB} (V)	T_A = 25°C Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL},	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	2.5	0.25	
	B to A		1.8	3.3	0.25	V
			2.5	3.3	0.6	
	Quiet Output Dynamic Peak V_{OL},	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	2.5	0.6	
	A to B		1.8	3.3	0.8	V
			2.5	3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL},	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	2.5	–0.25	
	B to A		1.8	3.3	–0.25	V
			2.5	3.3	–0.6	
	Quiet Output Dynamic Valley V_{OL},	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	2.5	–0.6	
	A to B		1.8	3.3	–0.8	V
			2.5	3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH},	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	2.5	1.9	
	A to B		1.8	3.3	2.2	V
			2.5	3.3	2.2	
V_{OHV}	Quiet Output Dynamic Valley V_{OH},	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	2.5	1.5	
	B to A		1.8	3.3	1.5	V
			2.5	3.3	1.9	

Capacitance

Symbol	Parameter	Conditions	T_A = +25°C Typical	Units
C_{IN}	Input Capacitance	V_{CCA} = 2.5V, V_{CCB} = 3.3V, V_I = 0V or $V_{CCA/B}$	6	pF
$C_{I/O}$	Input/Output Capacitance	V_{CCA} = 2.5V, V_{CCB} = 3.3V, V_I = 0V or $V_{CCA/B}$	7	pF
C_{PD}	Power Dissipation Capacitance	V_{CCA} = 2.5V, V_{CCB} = 3.3V, V_I = 0V or $V_{CCA/B}$ f = 10 MHz	20	pF

AC Loading and Waveforms

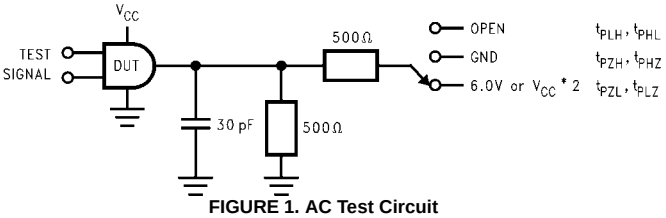


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	OPEN
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

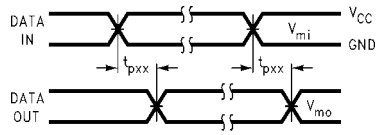


FIGURE 2. Waveform for Inverting and Non-inverting Functions
$t_R = t_F \leq$ 2.0 ns, 10% to 90%

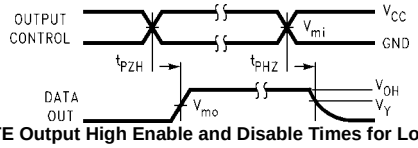


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic
$t_R = t_F \leq$ 2.0 ns, 10% to 90%

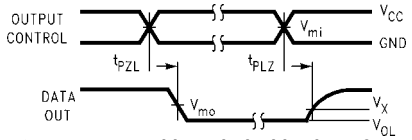
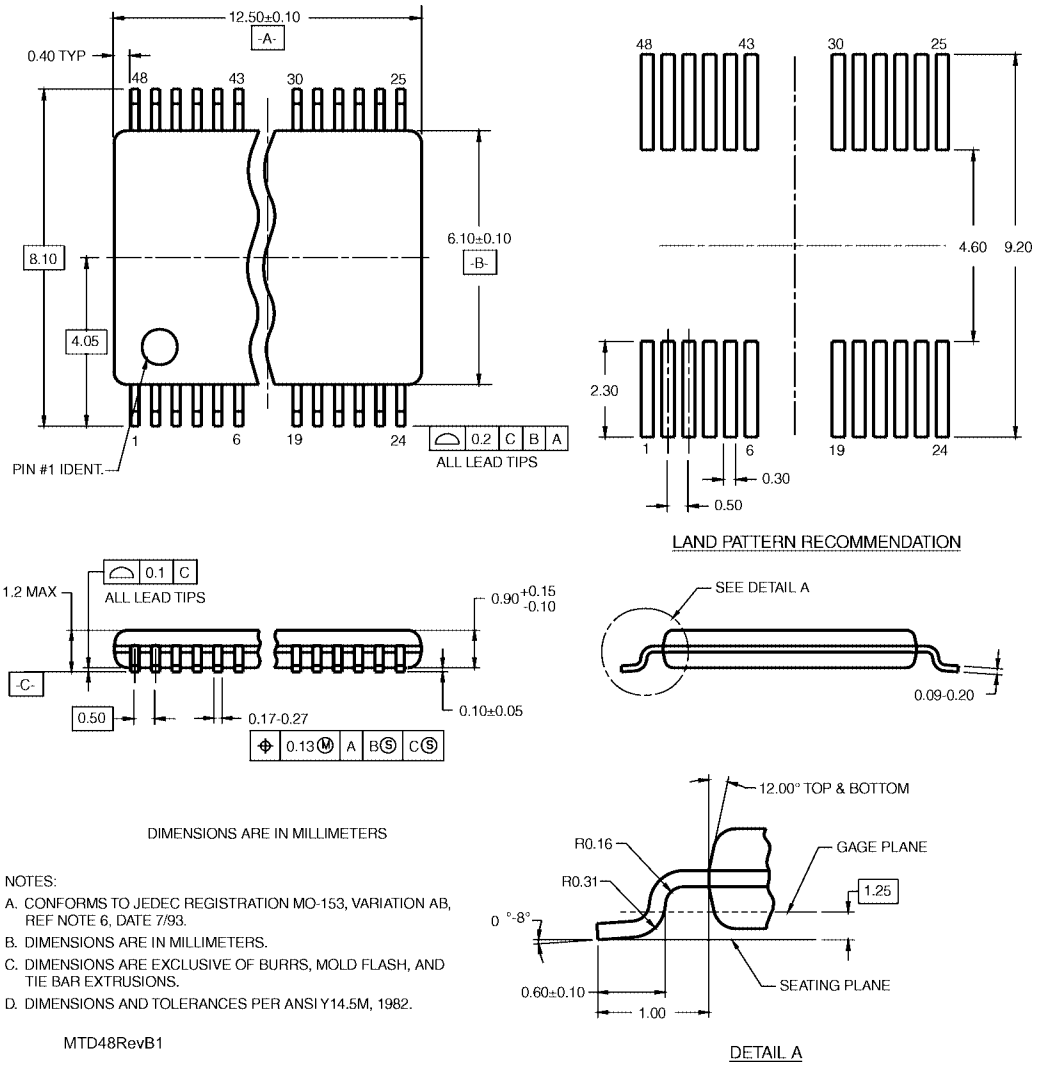


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic
$t_R = t_F \leq$ 2.0 ns, 10% to 90%

Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1998
Revised April 1999

74VCX16500
Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16500 is an 18-bit universal bus transceiver which combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and $\overline{OEBA}$), latch-enable (LEAB and LEBA), and clock ($\overline{CLKAB}$ and $\overline{CLKBA}$) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if $\overline{CLKAB}$ is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the HIGH-to-LOW transition of $\overline{CLKAB}$. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in a high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, LEBA, and $\overline{CLKBA}$. The output enables are complementary (OEAB is active HIGH and $\overline{OEBA}$ is active LOW).

The VCX16500 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16500 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (A to B, B to A)
  - 2.9 ns max for 3.0V to 3.6V V_{CC}
  - 3.5 ns max for 2.3V to 2.7V V_{CC}
  - 7.0 ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

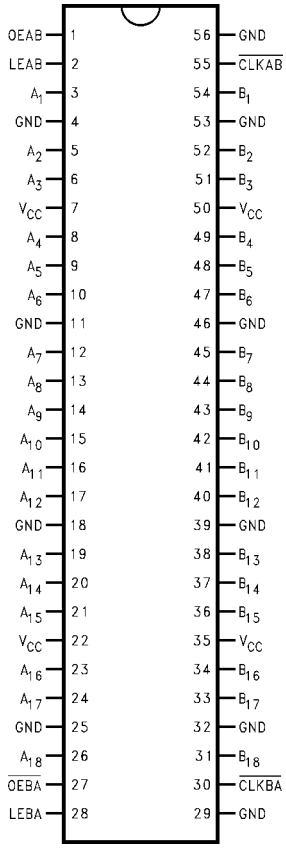
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OEBA}$ should be tied to V_{CC} through a pull-up resistor and OEAB should be tied to GND through a pull-down resistors; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16500MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
OEAB	Output Enable Input for A to B Direction (Active HIGH)
$\overline{OEBA}$	Output Enable Input for B to A Direction (Active LOW)
LEAB, LEBA	Latch Enable Inputs
$\overline{CLKAB}$, $\overline{CLKBA}$	Clock Inputs
A_1–A_{18}	Side A Inputs or 3-STATE Outputs
B_1–B_{18}	Side B Inputs or 3-STATE Outputs

Function Table (Note 2)

Inputs				Outputs
OEAB	**LEAB**	**$\overline{CLKAB}$**	**A_n**	**B_n**
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↓	L	L
H	L	↓	H	H
H	L	H	X	B_0 (Note 3)
H	L	L	X	B_0 (Note 4)

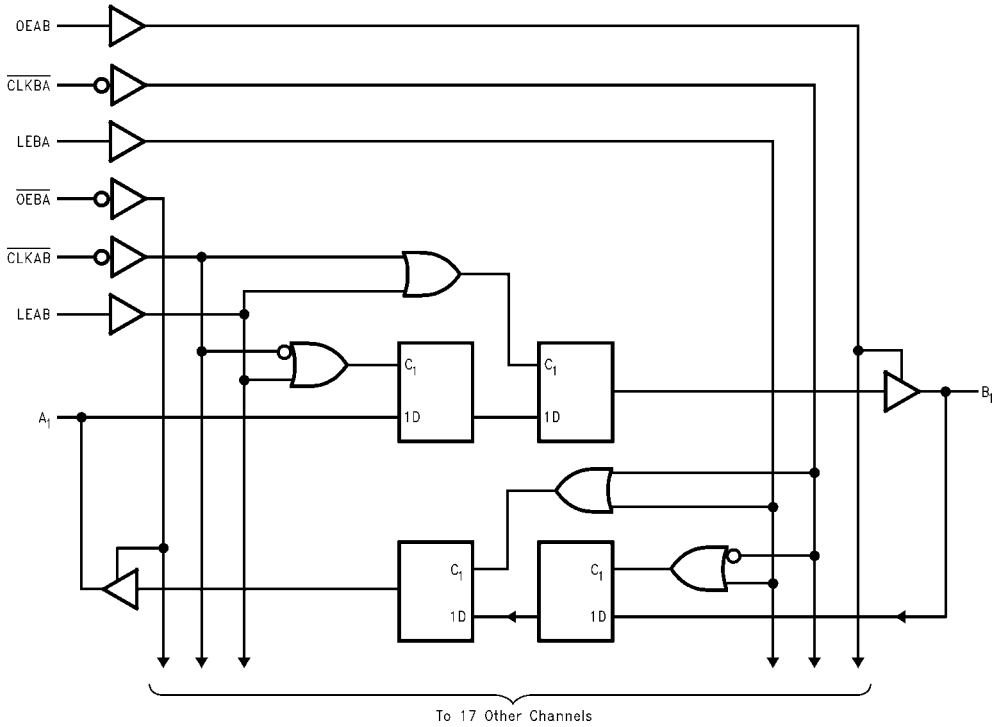
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{OEBA}$, LEBA and $\overline{CLKBA}$. $\overline{OEBA}$ is active LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Note 4: Output level before the indicated steady-state input conditions were established, provided that $\overline{CLKAB}$ was LOW before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings (Note 5)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 6)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per	
Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 5: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 8)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \leq V_{CC} \leq 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	μA
I_{OFF}	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 9)	2.3–2.7		±20	

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \leq V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 10)	1.65 - 2.3		±20	

Note 10: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 11)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL} t_{PLH}	Propagation Delay Bus to Bus	0.6	2.9	0.8	3.5	1.5	7.0	ns
t_{PHL} t_{PLH}	Propagation Delay Clock to Bus	0.6	4.2	0.8	5.3	1.5	9.8	ns
t_{PHL} t_{PLH}	Propagation Delay LE to Bus	0.6	3.8	0.8	4.9	1.5	9.8	ns
t_{PZL} t_{PZH}	Output Enable Time	0.6	3.8	0.8	4.9	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time	0.6	3.7	0.8	4.2	1.5	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 12)		0.5		0.5		0.75	ns

Note 11: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.25 0.6 0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	–0.25 –0.6 –0.8	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.5 1.9 2.2	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC} $V_{CC} = 1.8V$, 2.5V, or 3.3V,	6	pF
$C_{I/O}$	Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

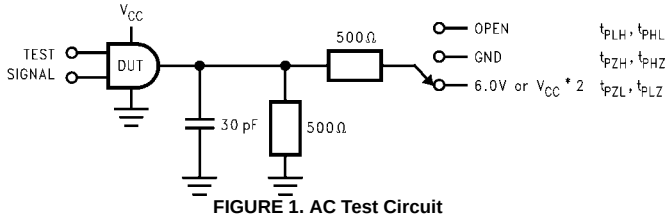


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8 ± 0.15V
t_{PZH}, t_{PHZ}	GND

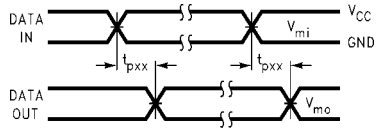


FIGURE 2. Waveform for Inverting and Non-inverting Functions

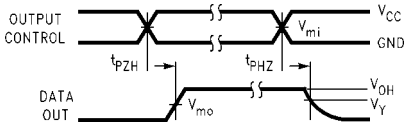


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

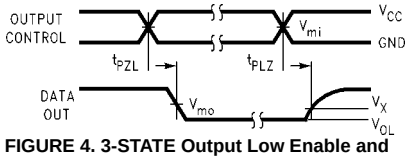


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

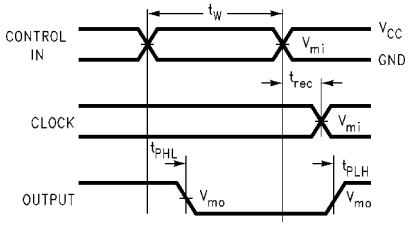


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

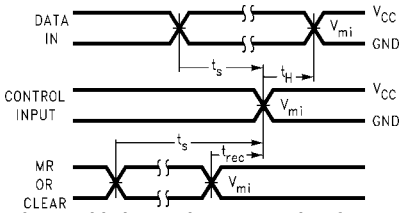
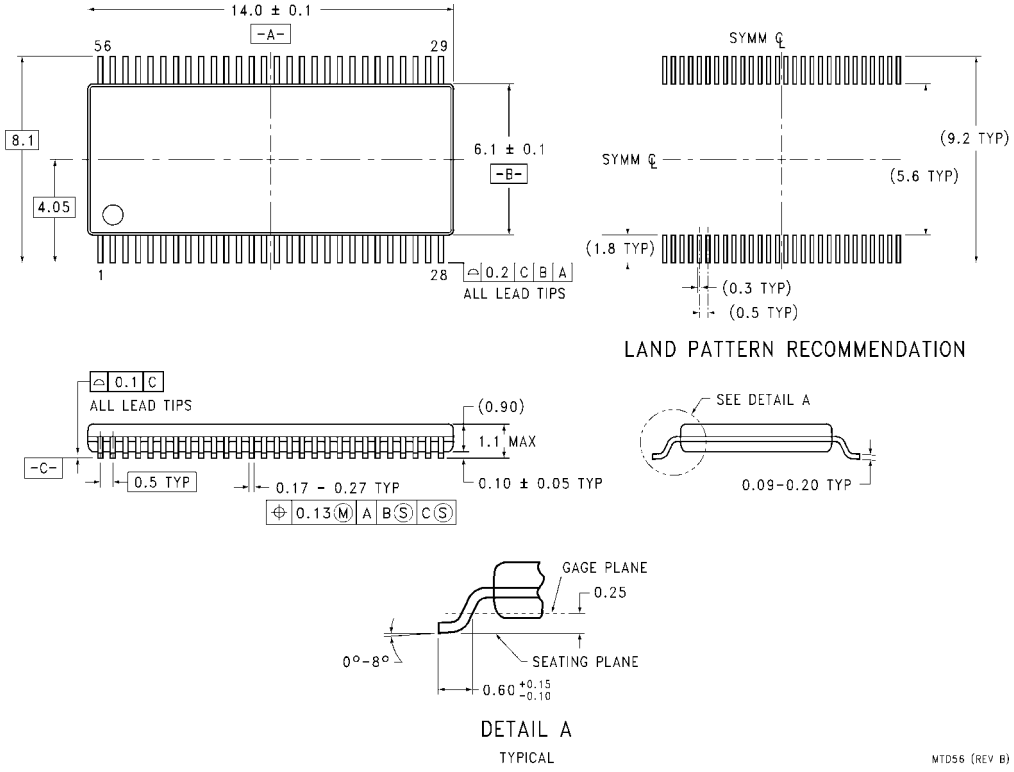


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8 ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1998
Revised April 1999

74VCX16501

Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16501 is an 18-bit universal bus transceiver which combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and $\overline{\text{OEBA}}$), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in a high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{\text{OEBA}}$, LEBA, and CLKBA. The output enables are complementary (OEAB is active HIGH and $\overline{\text{OEBA}}$ is active LOW).

The VCX16501 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The VCX16501 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (A to B, B to A)
  - 2.9 ns max for 3.0V to 3.6V V_{CC}
  - 3.5 ns max for 2.3V to 2.7V V_{CC}
  - 7.0 ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

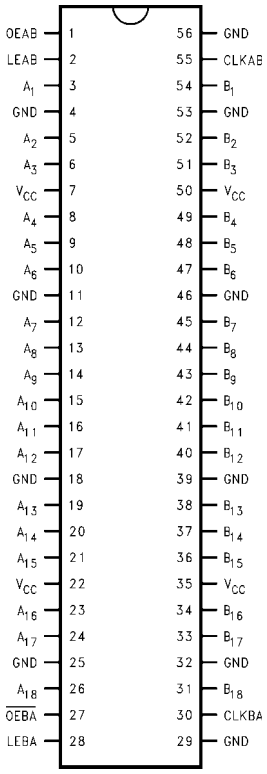
Note 1: To ensure the high-impedance state during power up or power down, $\overline{\text{OEBA}}$ should be tied to V_{CC} through a pull-up resistor and OEAB should be tied to GND through a pull-down resistor; the minimum value of the resistors is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16501MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
OEAB	Output Enable Input for A to B Direction (Active HIGH)
$\overline{OEBA}$	Output Enable Input for B to A Direction (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
A_1–A_{18}	Side A Inputs or 3-STATE Outputs
B_1–B_{18}	Side B Inputs or 3-STATE Outputs

Function Table (Note 2)

Inputs				Outputs
OEAB	**LEAB**	**CLKAB**	**A_n**	**B_n**
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↑	L	L
H	L	↑	H	H
H	L	H	X	B_0 (Note 3)
H	L	L	X	B_0 (Note 4)

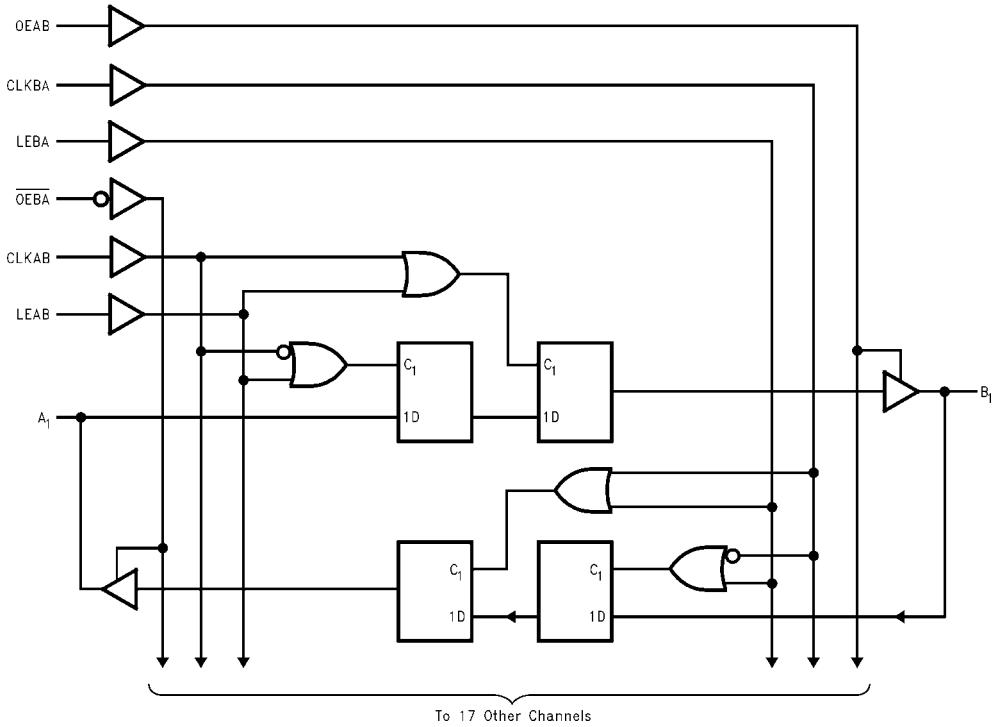
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{OEBA}$, LEBA and CLKBA. $\overline{OEBA}$ is active LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings (Note 5)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-Stated	−0.5V to +4.6V
Outputs Active (Note 6)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per	
Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 5: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 8)	2.7 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7 – 3.6		750	µA

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3 – 2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3 – 2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3 – 2.7		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 9)	2.3 – 2.7		±20	

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 10)	1.65 - 2.3		±20	

Note 10: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 11)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL} t_{PLH}	Propagation Delay Bus to Bus	0.6	2.9	0.8	3.5	1.5	7.0	ns
t_{PHL} t_{PLH}	Propagation Delay Clock to Bus	0.6	3.5	0.8	4.4	1.5	8.8	ns
t_{PHL} t_{PLH}	Propagation Delay LE to Bus	0.6	3.8	0.8	4.9	1.5	9.8	ns
t_{PZL} t_{PZH}	Output Enable Time	0.6	3.8	0.8	4.9	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time	0.8	3.7	0.8	4.2	0.8	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 12)		0.5		0.5		0.75	ns

Note 11: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.25 0.6 0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	−0.25 −0.6 −0.8	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.5 1.9 2.2	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC} $V_{CC} = 1.8V$, 2.5V, or 3.3V,	6	pF
$C_{I/O}$	Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

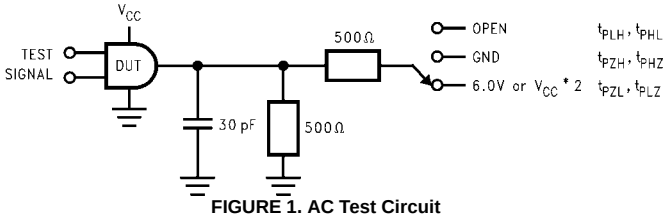


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8 ± 0.15V
t_{PZH}, t_{PHZ}	GND

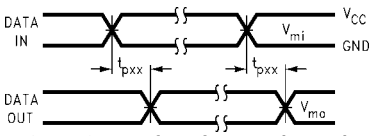


FIGURE 2. Waveform for Inverting and Non-inverting Functions

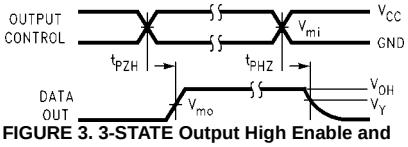


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

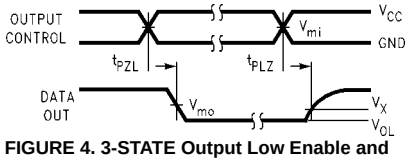


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

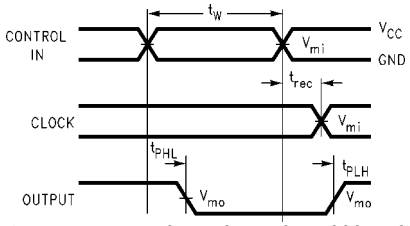


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

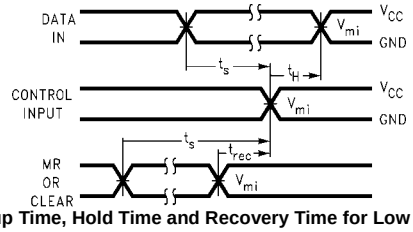
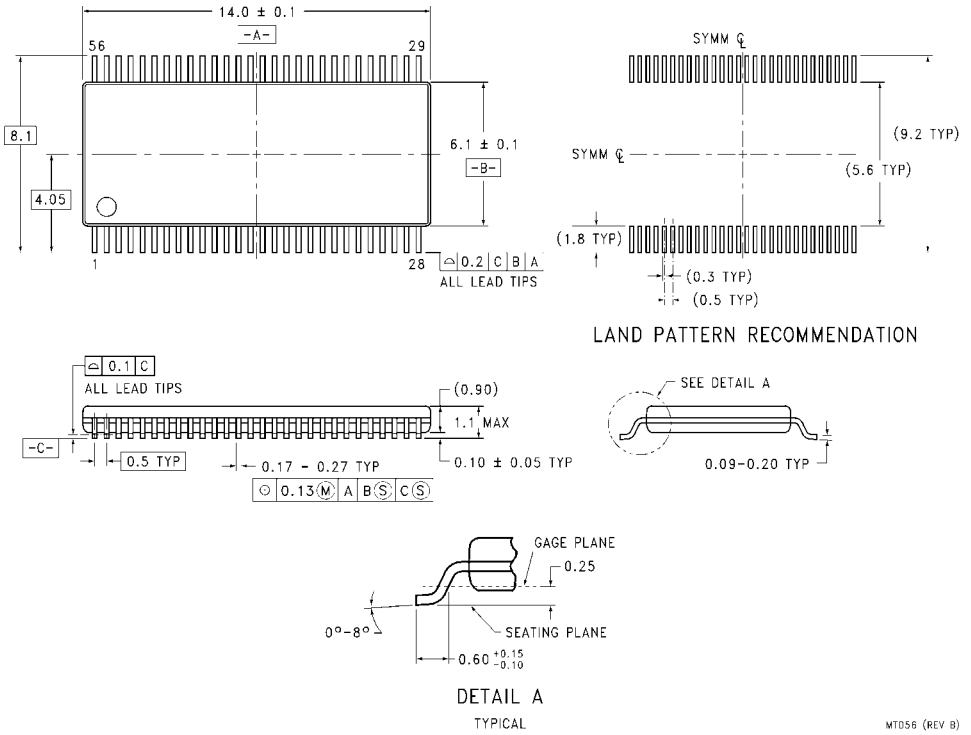


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8 ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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March 1998
Revised April 1999

74VCX16601
Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16601 is an 18-bit universal bus transceiver which combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable ($\overline{OEAB}$ and $\overline{OEBA}$), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable ($\overline{CLKENAB}$ and $\overline{CLKENBA}$) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH-to-LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. When $\overline{OEAB}$ is LOW, the outputs are active. When $\overline{OEAB}$ is HIGH, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, LEBA, CLKBA and $\overline{CLKENBA}$.

The VCX16601 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The VCX16601 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (A to B, B to A)
  - 2.9 ns max for 3.0V to 3.6V V_{CC}
  - 3.5 ns max for 2.3V to 2.7V V_{CC}
  - 7.0 ns max for 1.65V 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

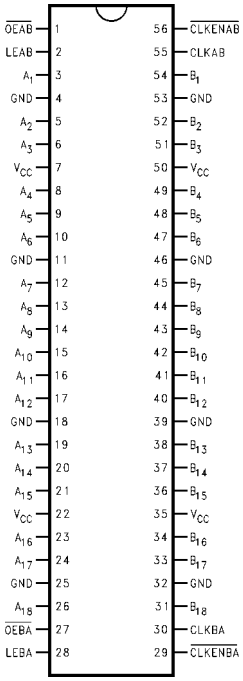
Order Number	Package Number	Package Description
74VCX16601MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
$\overline{CLKENAB}$, $\overline{CLKENBA}$	Clock Enable Inputs
A_1–A_{18}	Side A Inputs or 3-STATE Outputs
B_1–B_{18}	Side B Inputs or 3-STATE Outputs

Connection Diagram



Function Table (Note 2)

Inputs					Outputs
$\overline{CLKENAB}$	$\overline{OEAB}$	LEAB	CLKAB	A_n	B_n
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	B_0 (Note 3)
H	L	L	X	X	B_0 (Note 3)
L	L	L	↑	L	L
L	L	L	↑	H	H
L	L	L	L	X	B_0 (Note 3)
L	L	L	H	X	B_0 (Note 4)

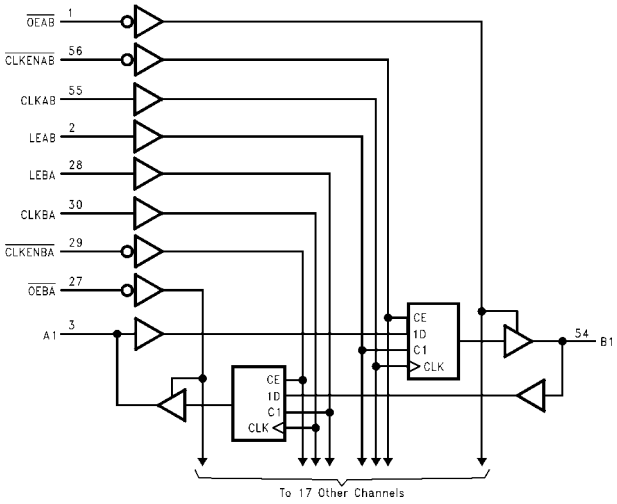
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{OEBA}$, LEBA, CLKBA, and $\overline{CLKENBA}$.

Note 3: Output level before the indicated steady-state input conditions were established.

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings (Note 5)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-Stated	−0.5V to +4.6V
Outputs Active (Note 6)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 5: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V; V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 8)	2.7 – 3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7 – 3.6		750	µA

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = –6 mA	2.3	2.0		
		I_{OH} = –12 mA	2.3	1.8		
		I_{OH} = –18 mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3 – 2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 9)	2.3 – 2.7		±20	

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = –6 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 10)	1.65 - 2.3		±20	

Note 10: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 11)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL} t_{PLH}	Propagation Delay Bus to Bus	0.8	2.9	1.0	3.5	1.5	7.0	ns
t_{PHL} t_{PLH}	Propagation Delay Clock to Bus	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PHL} t_{PLH}	Propagation Delay LE to Bus	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PZL} t_{PZH}	Output Enable Time	0.8	3.8	1.0	4.9	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 12)		0.5		0.5		0.75	ns

Note 11: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.25 0.6 0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	–0.25 –0.6 –0.8	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.5 1.9 2.2	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC} $V_{CC} = 1.8V$, 2.5V, or 3.3V	6	pF
$C_{I/O}$	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

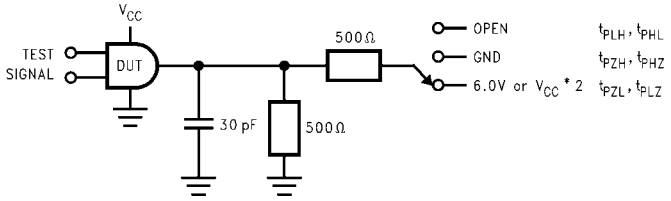


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

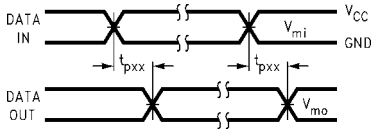


FIGURE 2. Waveform for Inverting and Non-inverting Functions

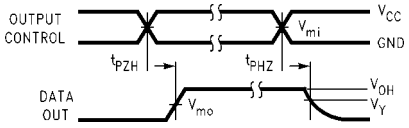


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

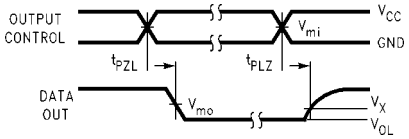


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

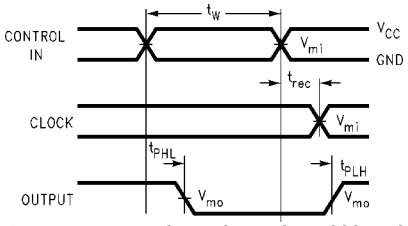


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

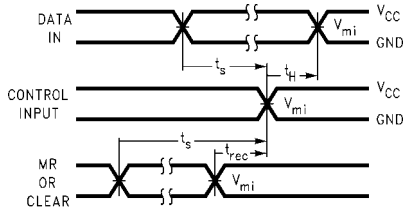
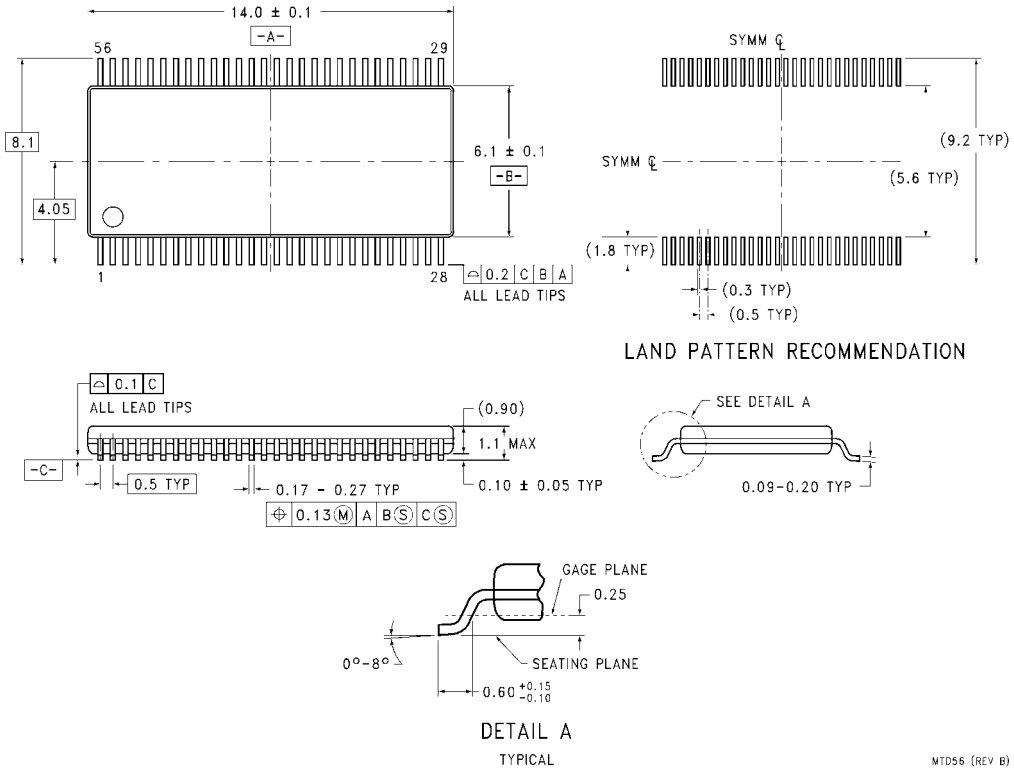


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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March 1998
Revised April 1999

74VCX16721

Low Voltage 20-Bit D-Type Flip-Flops with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16721 contains twenty non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications.

The 74VCX16721 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16721 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.8V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (CLK to O_n)
  - 3.5 ns max for 3.0V to 3.6V V_{CC}
  - 4.4 ns max for 2.3V to 2.7V V_{CC}
  - 8.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

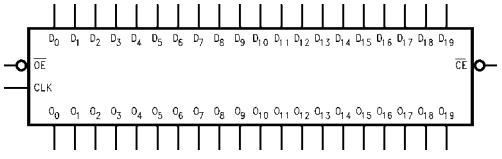
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16721MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

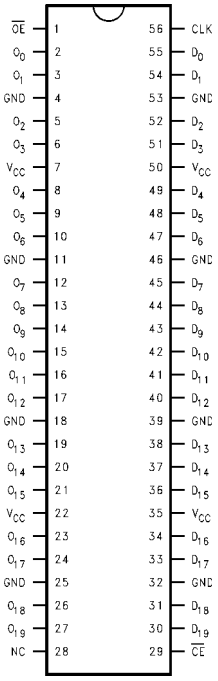
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
CLK	Clock Input
D_0–D_{19}	Inputs
O_0–O_{19}	Outputs
$\overline{CE}$	Clock Enable Input (Active LOW)

Connection Diagram



Truth Table

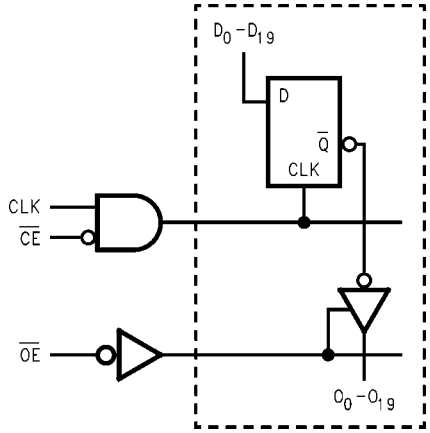
CLK	$\overline{CE}$	$\overline{OE}$	D_0–D_{19}	O_0–O_{19}
X	X	H	X	Z
X	H	L	X	O_0
⌐	L	L	L	L
⌐	L	L	H	H
L or H	L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before LOW-to-HIGH transition of Clock
⌐ = LOW-to-HIGH transition

Functional Description

The VCX16721 contains twenty D-type flip-flops with 3-STATE standard outputs. The twenty flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-HIGH Clock (CLK) transition, when the Clock-Enable ($\overline{CE}$) is LOW. The 3-STATE standard outputs are controlled by the Output-Enable ($\overline{OE}$). When $\overline{OE}$ is HIGH, the standard outputs are in high impedance mode but this does not interfere with entering new data into the flip-flops.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature	
(T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = −6 mA	2.3	2.0		V
		I_{OH} = −12 mA	2.3	1.8		V
		I_{OH} = −18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = −6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay CLK to O_n	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	4.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

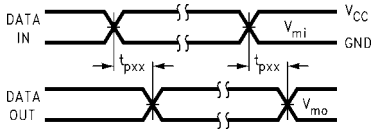
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

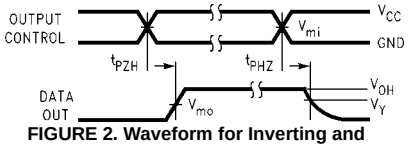


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

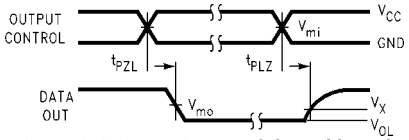


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

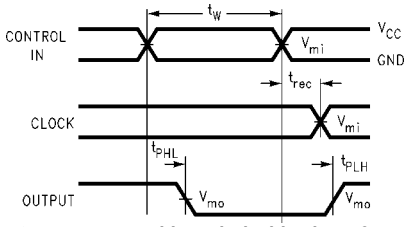


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

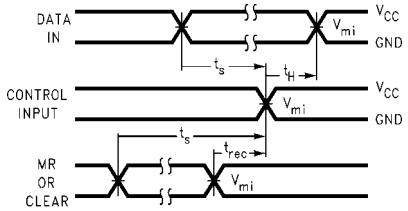


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

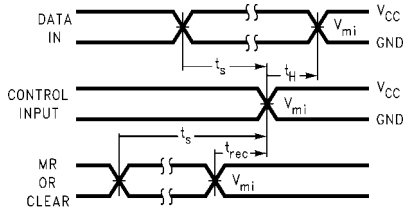
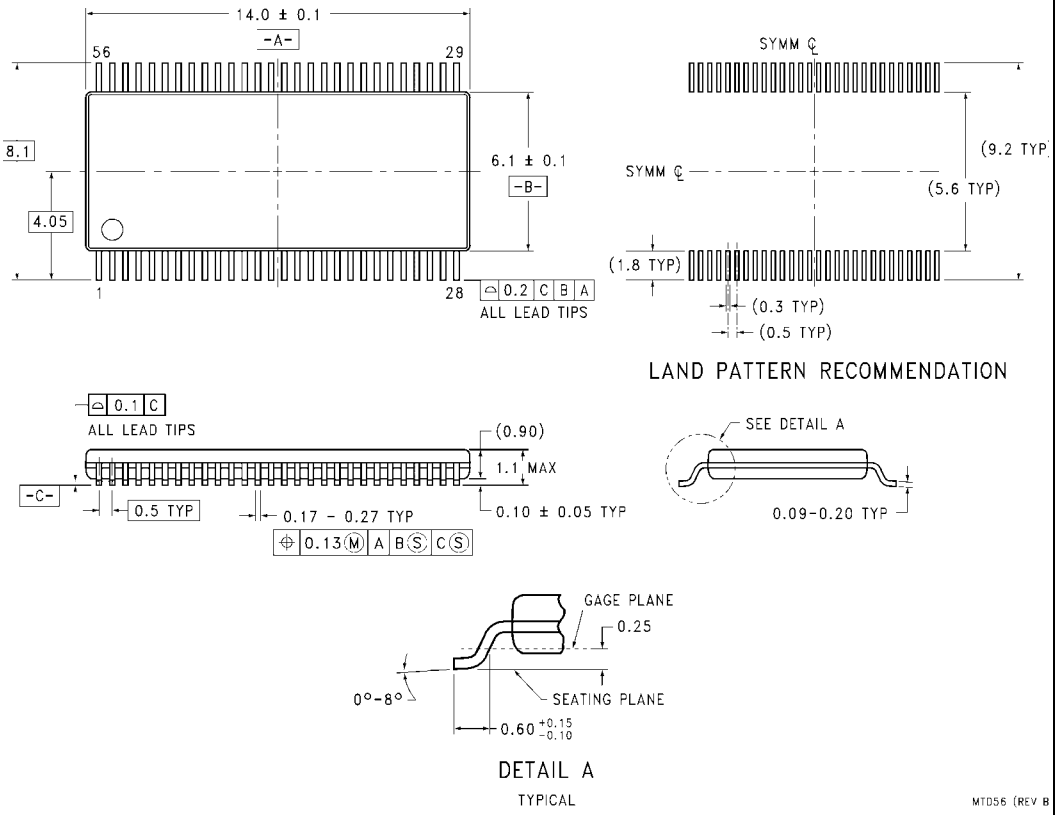


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

FAIRCHILD SEMICONDUCTOR™

February 1999
Revised April 1999

74VCX16722
Low Voltage 22-Bit Register with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16722 low voltage 22-bit register contains twenty-two non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The design has been optimized for use with JEDEC compliant 200 pin DIMM modules.

The 74VCX16722 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16722 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} specifications provided
- 3.6V tolerant inputs and outputs
- t_{PD} (CLK to O_n)
  - 3.6ns max for 3.0V to 3.6V V_{CC}
  - 4.6ns max for 2.3V to 2.7V V_{CC}
  - 9.2ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Meets JEDEC registered module specifications
- Static Drive (I_{OH}/I_{OL})
  - ±24mA @ 3.0V
  - ±18mA @ 2.3V
  - ±6mA @ 1.65V
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

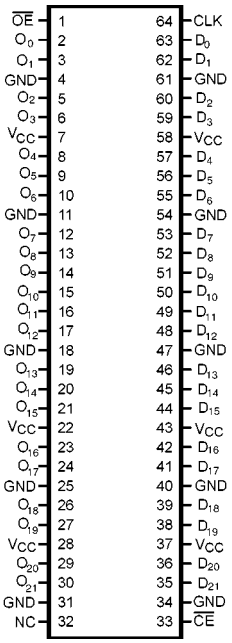
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16722MTD	MTD64	64-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
$\overline{CE}$	Clock Enable Input (Active Low)
CLK	Clock Input
D_1 - D_{21}	Data Inputs
O_1 - O_{21}	3-STATE Outputs

Truth Table

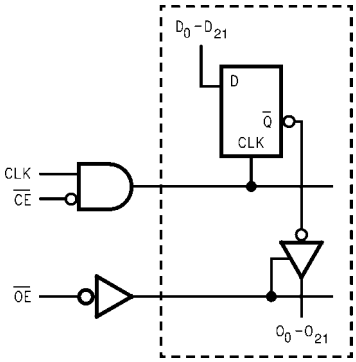
CLK	$\overline{CE}$	$\overline{OE}$	D_0-D_{21}	O_0-O_{21}
X	X	H	X	Z
X	H	L	X	O_0
⌐	L	L	L	L
⌐	L	L	H	H
L or H	L	L	X	O_0

H = HIGH Voltage Level
L = LOW Level Voltage
X = Immaterial (HIGH or LOW, Inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before LOW-to-HIGH transition of Clock
⌐ = LOW-to-HIGH transition

Functional Description

The VCX16722 contains twenty-two D-type flip-flops with 3-STATE standard outputs. The twenty-two flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-HIGH Clock (CLK) transition, when the Clock-Enable ($\overline{CE}$) is LOW. The 3-STATE standard outputs are controlled by the Output-Enable ($\overline{OE}$). When $\overline{OE}$ is HIGH, the standard outputs are in high impedance mode but this does not interfere with entering new data into the flip-flops.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3–2.7		±20	

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
		$I_{OL} = 6$mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Propagation Delay Clock to Bus	1.3	3.6	1.5	4.6	2.0	9.2	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.6	3.5	0.8	4.5	1.5	9.0	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.6	3.2	0.8	4.2	1.5	7.6	ns
t_S	Setup Time	2.0		2.0		3.0		ns
t_H	Hold Time	0.0		0.0		0.5		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For C_L=50 pF, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

AC Electrical Characteristics Over Load (Note 10)

Symbol	Parameter	$T_A = -0°C$ to $+70°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.3V$				Units
		$C_L = 0$ pF		$C_L = 50$ pF		
		Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay Clock to Bus	1.1	2.5	1.9	3.9	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.7	2.4	1.0	3.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.7	2.1	1.0	3.5	ns
t_S	Setup Time	2.0		2.0		ns
t_H	Hold Time	0.0		0.0		ns
t_W	Pulse Width	1.5		1.5		ns

Note 10: This parameter is guaranteed by characterization but not tested.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.25	V
			2.5	−0.6	
			3.3	−0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V, or 3.3V,	3.5	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	5.5	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	13	pF

I_{OUT} - V_{OUT} Characteristics

I_{OH} versus V_{OH}

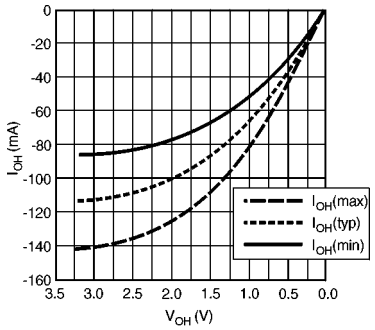


FIGURE 1. Characteristics for Output - Pull Up Driver

I_{OL} versus V_{OL}

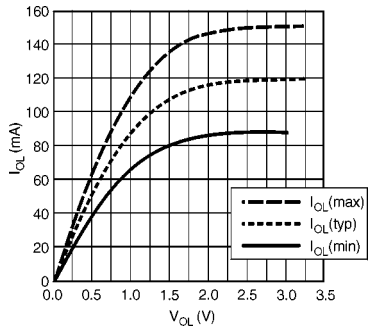


FIGURE 2. Characteristics for Output - Pull Down Driver

AC Loading and Waveforms

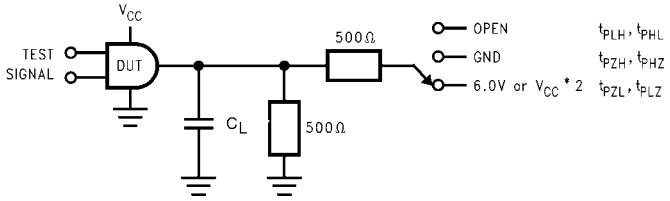


FIGURE 3. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V to ± 0.15V
t_{PZH}, t_{PHZ}	GND

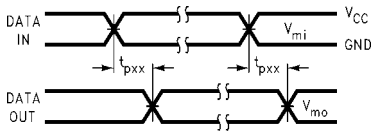


FIGURE 4. Waveform for Inverting and Non-inverting Functions
$t_r = t_f \leq$ 2.0ns, 10% to 90%

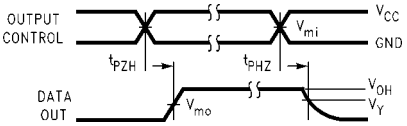


FIGURE 5. 3-STATE Output High Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

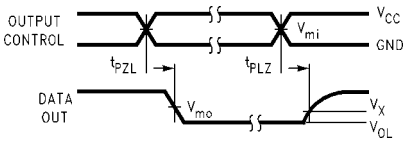
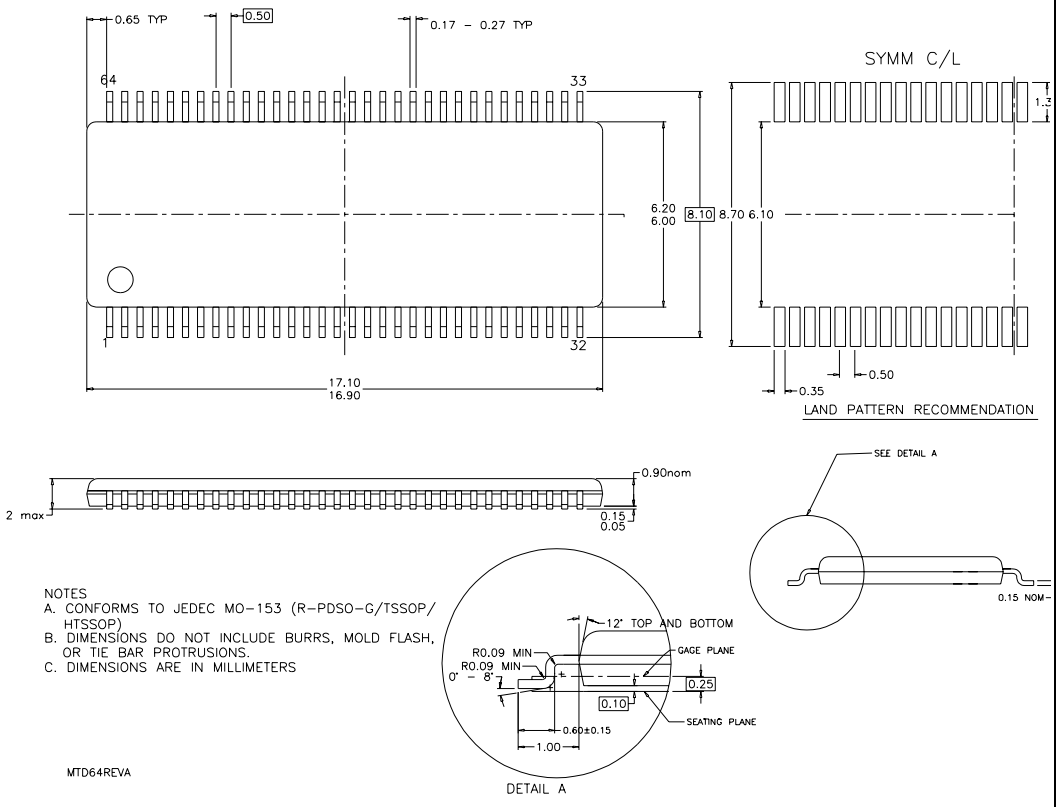


FIGURE 6. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8 ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



64-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD64

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
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FAIRCHILD SEMICONDUCTOR™

March 1998
Revised April 1999

74VCX16821

Low Voltage 20-Bit D-Type Flip-Flops with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16821 contains twenty non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications.

The 74VCX16821 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16821 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 3.5 ns max for 3.0V to 3.6V V_{CC}
  - 4.4 ns max for 2.3V to 2.7V V_{CC}
  - 8.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

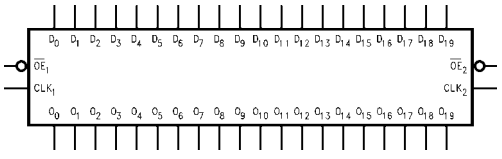
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX16821MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

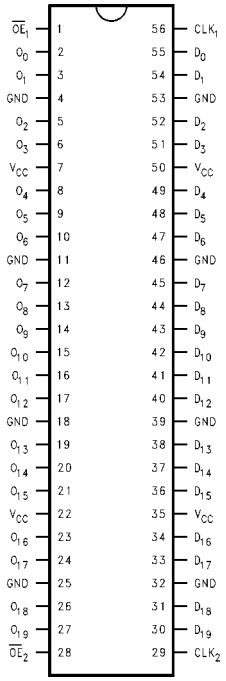
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CLK_n	Clock Input
D_0–D_{19}	Inputs
O_0–O_{19}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
CLK_1	$\overline{OE}_1$	D_0–D_9	O_0–O_9
X	H	X	Z
↗	L	L	L
↗	L	H	H
L or H	L	X	O_0

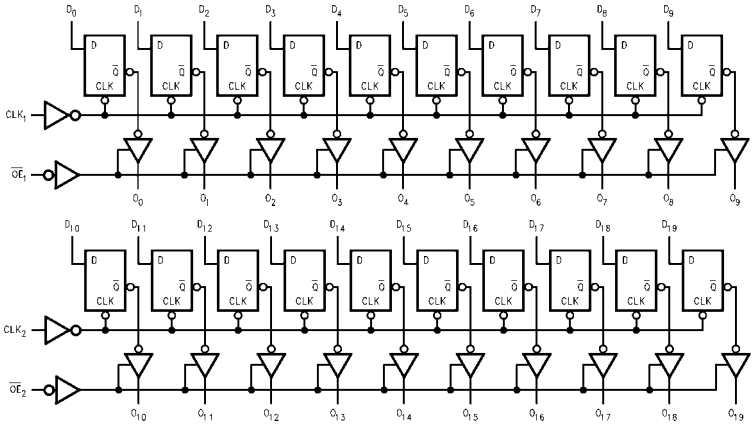
Inputs			Outputs
CLK_2	$\overline{OE}_2$	D_{10}–D_{19}	O_{10}–O_{19}
X	H	X	Z
↗	L	L	L
↗	L	H	H
L or H	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before LOW-to-HIGH transition of Clock
↗ = LOW-to-HIGH transition

Functional Description

The VCX16821 contains twenty D-type flip-flops with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of each other. Control pins can be shorted together to obtain full 20-bit operation. The following description applies to each byte. The twenty flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CLK) transition. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the flip-flops.

Logic Diagrams



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = −6 mA	2.3	2.0		V
		I_{OH} = −12 mA	2.3	1.8		V
		I_{OH} = −18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		0.35 × V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = −6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay CLK to O_n	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.7	1.0	4.7	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

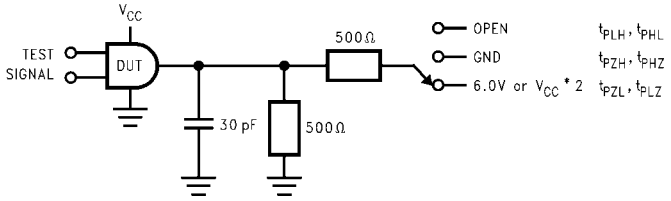
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

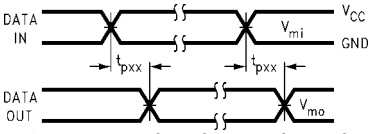


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

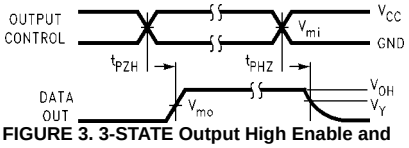


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

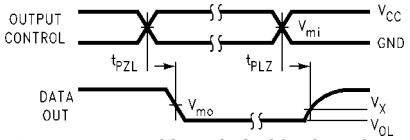


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

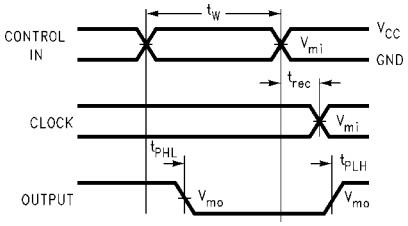


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

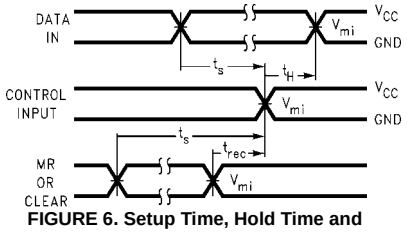
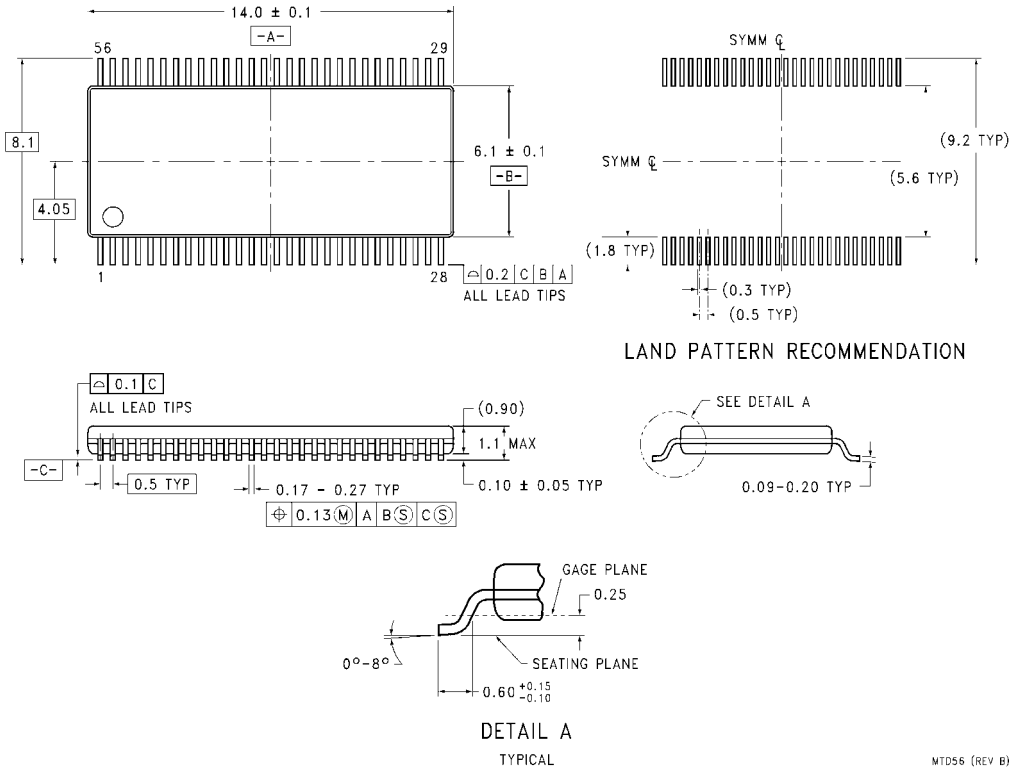


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1998
Revised April 1999

74VCX16827
Low Voltage 20-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16827 contains twenty non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver carrying parity. The device is byte controlled. Each byte has NOR output enables for maximum control flexibility.

The 74VCX16827 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16827 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.5 ns max for 3.0V to 3.6V V_{CC}
  - 3.0 ns max for 2.3V to 2.7V V_{CC}
  - 6.0 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

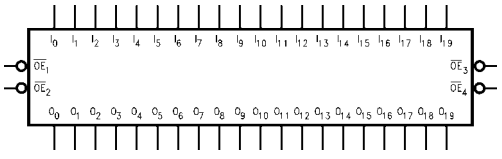
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16827MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

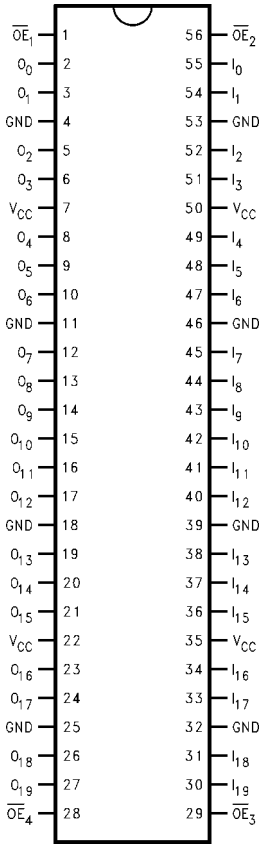
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{19}	Inputs
O_0–O_{19}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I_0–I_9	O_0–O_9
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

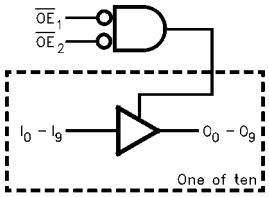
Inputs			Outputs
$\overline{OE}_3$	$\overline{OE}_4$	I_0–I_9	O_{10}–O_{19}
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

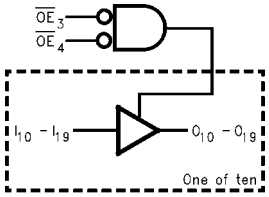
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX16827 contains twenty non-inverting buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by Output Enable ($\overline{OE}_n$) inputs. When $\overline{OE}_1$, and $\overline{OE}_2$ are LOW, O_0—O_{10} are in the 2-state mode. When either $\overline{OE}_1$ or $\overline{OE}_2$ are HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs. The same applies for byte two with $\overline{OE}_3$ and $\overline{OE}_4$.

Logic Diagrams





Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = –6 mA	2.3	2.0		V
		I_{OH} = –12 mA	2.3	1.8		V
		I_{OH} = –18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = –6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	4.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

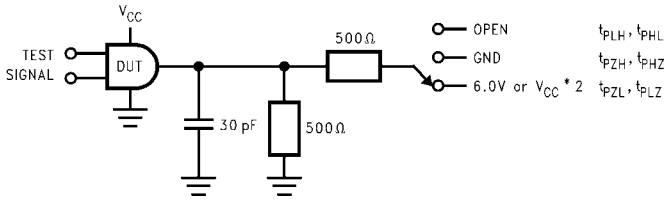
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

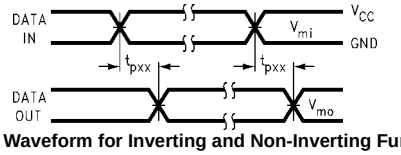


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

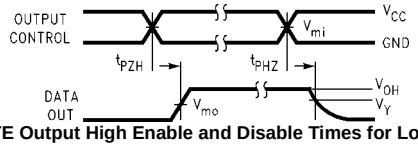


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

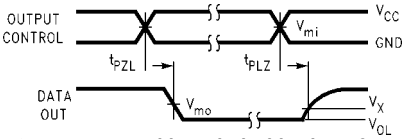
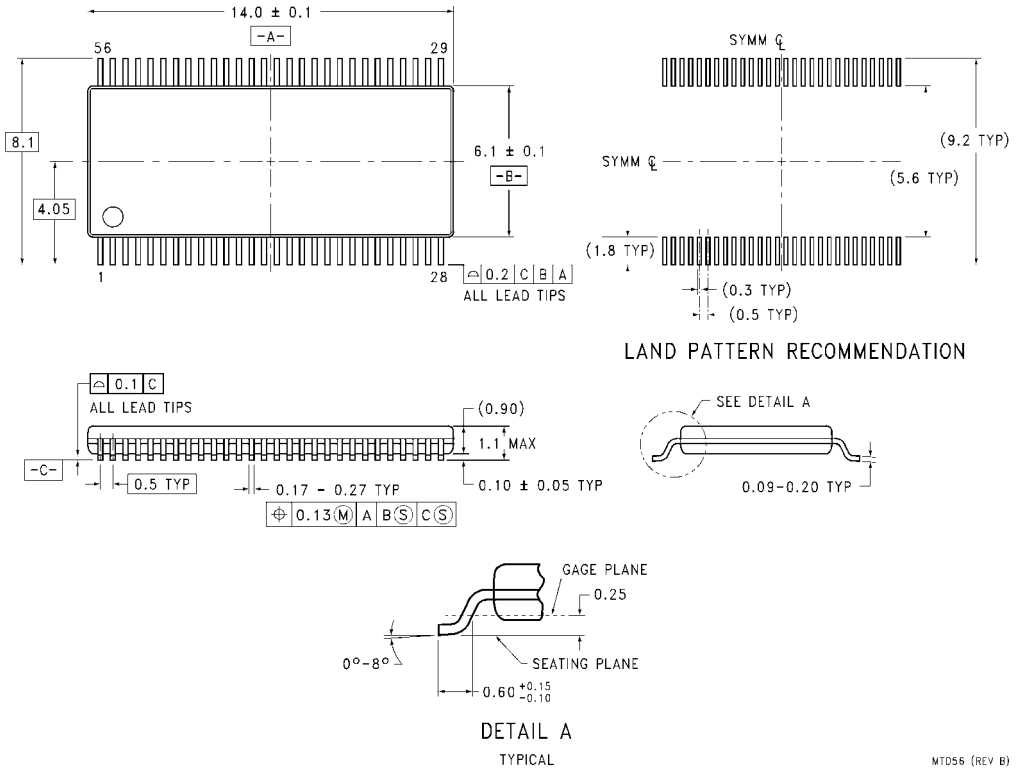


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

FAIRCHILD SEMICONDUCTOR™

October 1998
Revised April 1999

74VCX16835
Low Voltage 18-Bit Universal Bus Driver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16835 low voltage 18-bit universal bus driver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched and clocked modes.

Data flow is controlled by output-enable ($\overline{OE}$), latch-enable (LE), and clock (CLK) inputs. The device operates in Transparent Mode when LE is held HIGH. The device operates in clocked mode when LE is LOW and CLK is toggled. Data transfers from the Inputs (I_n) to Ouputs (O_n) on a Positive Edge Transition of the Clock. When $\overline{OE}$ is LOW, the output data is enabled. When $\overline{OE}$ is HIGH the output port is in a high impedance state.

The 74VCX16835 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16835 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 DIMM module specifications
- 1.65V–3.6V V_{CC} specifications provided
- 3.6V tolerant inputs and outputs
- t_{PD} (CP to O_n)
  - 4.2ns max for 3.0V to 3.6V V_{CC}
  - 5.2ns max for 2.3V to 2.7V V_{CC}
  - 9.2ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24mA @ 3.0V
  - ±18mA @ 2.3V
  - ±6mA @ 1.65V
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

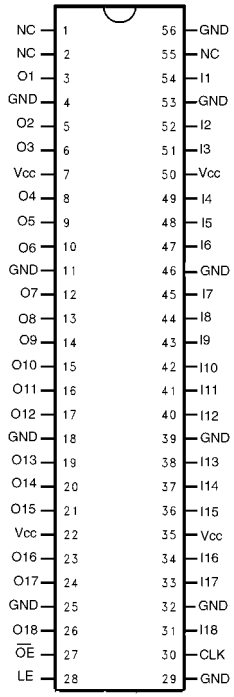
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} (OE to GND) through a pulldown resistor; the minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16835MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable Input
CP	Clock Input
I_1 - I_{18}	Data Inputs
O_1 - O_{18}	3-STATE Outputs

Function Table

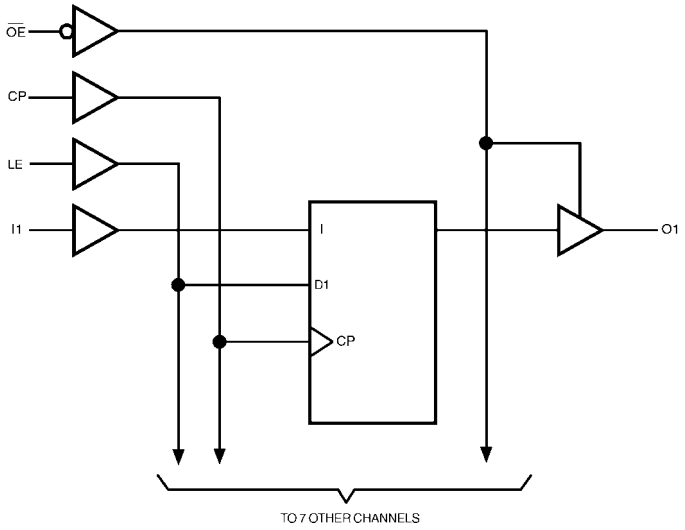
Inputs				Outputs
$\overline{OE}$	LE	CP	I_n	O_n
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	↑	L	L
L	L	↑	H	H
L	L	H	X	Io (Note 2)
L	L	L	X	Io (Note 3)

H = HIGH Voltage Level
L = LOW Level Voltage
X = Immaterial (HIGH or LOW, Inputs may not float)
Z = High Impedance

Note 2: Output level before the indicated steady-state input conditions were established provided that CP was HIGH before LE went LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Logic Diagram



Absolute Maximum Ratings (Note 4)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 5)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 6)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 4: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 7)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 - 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 - 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	2.3 -2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	2.3 - 2.7		0.2	V
		$I_{OL} = 12$mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 - 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3 - 2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 8)	2.3 - 2.7		±20	

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100$ µA	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100$ µA	1.65 - 2.3		0.2	V
		$I_{OL} = 6$mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 9)	1.65 - 2.3		±20	

Note 9: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Propagation Delay Bus to Bus	0.6	3.3	0.8	4.2	1.5	8.4	ns
t_{PHL}, t_{PLH}	Propagation Delay Clock to Bus	1.4	4.2	1.5	5.2	2.0	9.2	ns
t_{PHL}, t_{PLH}	Propagation Delay LE to Bus	0.6	3.8	0.8	4.9	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.6	3.8	0.8	4.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.6	3.9	0.8	4.5	1.5	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 11)		0.5		0.5		0.75	ns

Note 10: For CL=50pF, add approximately 300ps to the AC maximum specification.

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

AC Electrical Characteristics Over Load (Note 12)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.15V$				Units
		$C_L = 0$ pF		$C_L = 50$ pF		
		Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay Bus to Bus	0.7	2.1	1.0	3.6	ns
t_{PHL}, t_{PLH}	Prop Delay Clock to Bus	1.5	3.0	1.7	4.5	ns
t_{PHL}, t_{PLH}	Prop Delay LE to Bus	0.7	2.6	1.0	4.1	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.7	2.6	1.0	4.1	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.7	2.7	1.0	4.2	ns
t_{PHL}, t_{PLH}	SSO Prop Delay Clock to Bus (Note 13)	1.5	3.3			ns
t_S	Setup Time	1.5		1.5		ns
t_H	Hold Time	0.7		0.7		ns

Note 12: This parameter is guaranteed by characterization but not tested.

Note 13: SSO = Simultaneous Switching Output. Any output combination of LOW-to-HIGH and/or HIGH-to-LOW transition.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.35	V
			2.5	0.7	
			3.3	0.9	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.35	V
			2.5	−0.7	
			3.3	−0.9	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.3	V
			2.5	1.7	
			3.3	2.0	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V, or 3.3V,	3.5	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	5.5	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	13	pF

I_{OUT} - V_{OUT} Characteristics

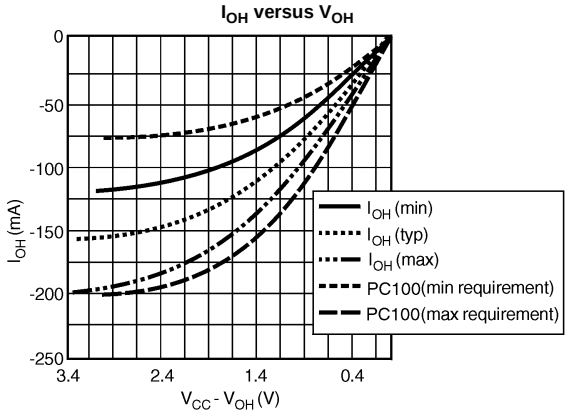


FIGURE 1. Characteristics for Output - Pull Up Driver

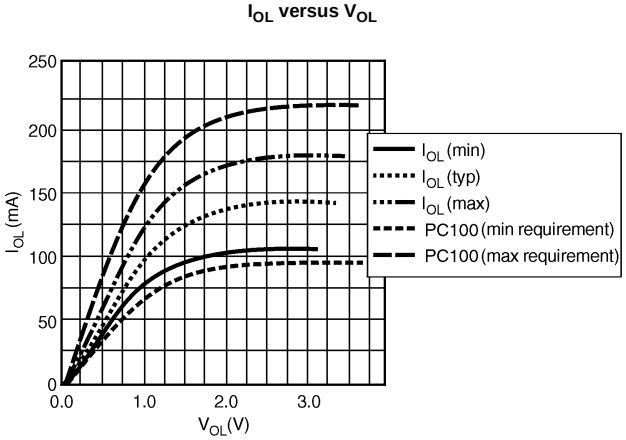


FIGURE 2. Characteristics for Output - Pull Down Driver

AC Loading and Waveforms

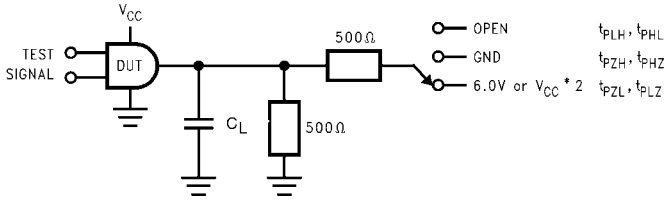


FIGURE 3. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V to ± 0.15V
t_{PZH}, t_{PHZ}	GND

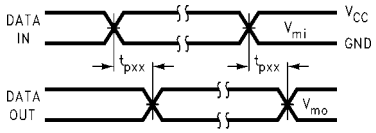


FIGURE 4. Waveform for Inverting and Non-inverting Functions
$t_r = t_f \leq$ 2.0ns, 10% to 90%

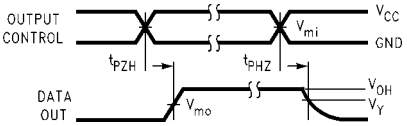


FIGURE 5. 3-STATE Output High Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

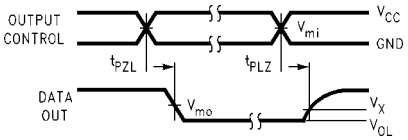
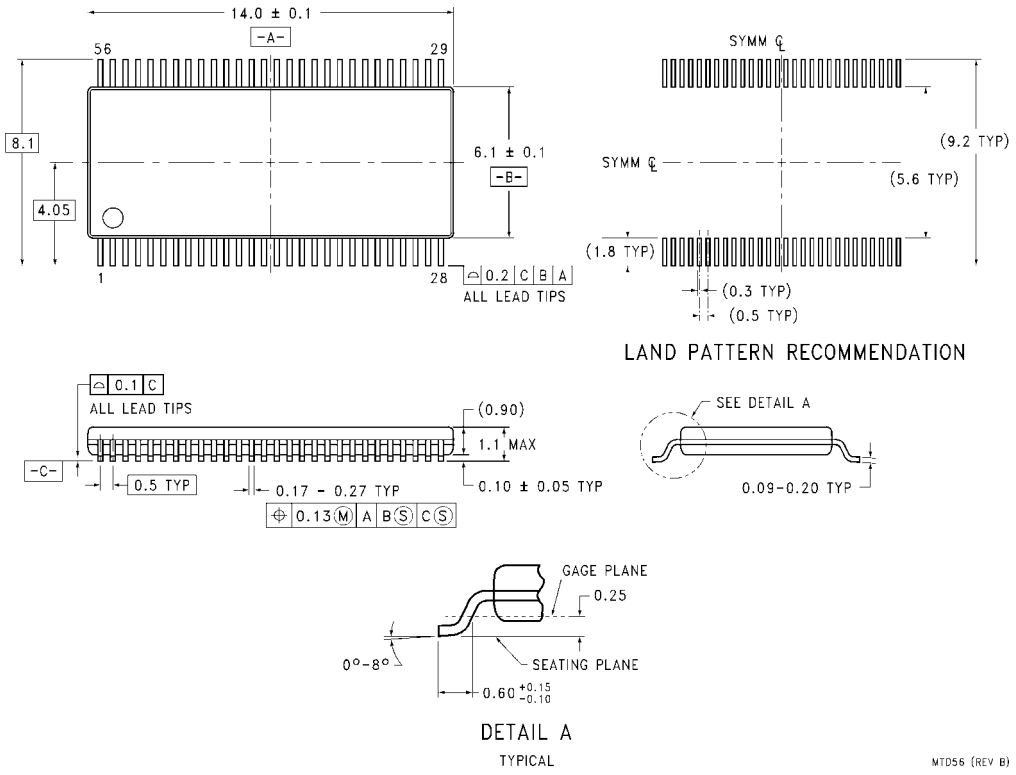


FIGURE 6. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8 ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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July 1997
Revised April 1999

74VCX16838
Low Voltage 16-Bit Selectable Register/Buffer with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16838 contains sixteen non-inverting selectable buffered or registered paths. The device can be configured to operate in a registered, or flow through buffer mode by utilizing the register enable (REGE) and Clock (CP) signals. The device operates in a 16-bit word wide mode. All outputs can be placed into 3-State through use of the $\overline{OE}$ Pin. These devices are ideally suited for buffered or registered 168 pin and 200 pin SDRAM DIMM memory modules.

The 74VCX16838 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16838 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 and PC133 DIMM module specifications
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (CP to O_n)
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 4.0 ns max for 2.3V to 2.7V V_{CC}
  - 8.0 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Ideal for SDRAM DIMM modules
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

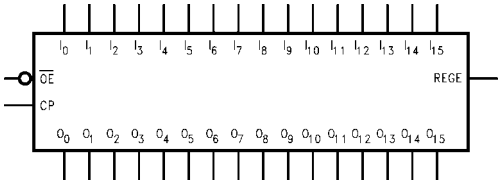
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16838MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

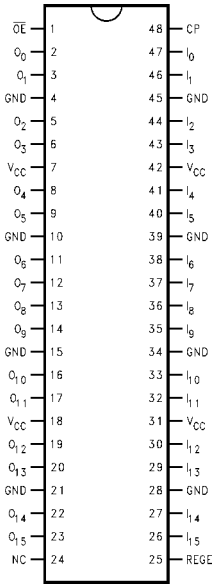
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
I_0–I_{15}	Inputs
O_0–O_{15}	Outputs
CP	Clock Pulse Input
REGE	Register Enable Input

Connection Diagram



Truth Table

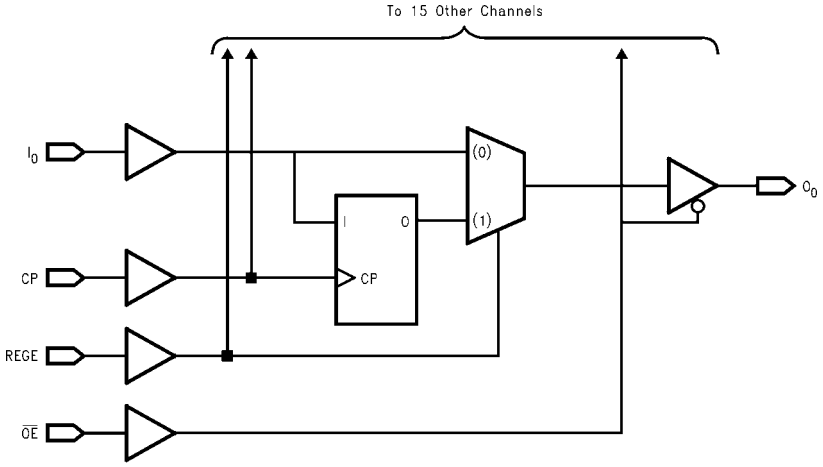
Inputs				Outputs
CP	REGE	I_n	$\overline{OE}$	O_n
↑	H	H	L	H
↑	H	L	L	L
X	L	H	L	H
X	L	L	L	L
X	X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX16838 consists of sixteen selectable non-inverting buffers or registers with word wide controls. Mode functionality is selected through operation of the CP and REGE pin as shown by the truth table. When REGE is held at a logic "1" the device operates as a 16-bit register. Data is transferred from I_n to O_n on the rising edge of the CP pin. When the REGE pin is held at a logic "0" the device operates in a flow through mode and data propagates directly from the I to the O outputs. All outputs can be 3-STATE by holding the $\overline{OE}$ pin at a logic "1."

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		V
		$I_{OH} = -12$ mA	2.3	1.8		V
		$I_{OH} = -18$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	V
		$I_{OL} = 18$ mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3–2.7		±20	μA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	μA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	0.8	2.5	1.0	3.5	1.5	7.0	ns
t_{PHL}, t_{PLH}	Prop Delay CP to O_n (REGE = 1)	0.8	3.0	1.0	4.0	1.5	8.0	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	0.8	3.0	1.0	4.0	1.5	8.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.7	1.5	9.4	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.9	1.5	7.0	ns
t_S	Setup Time	1.0		1.0		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} / t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Extended AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.3V$		Units
		$C_L = 50$ pF		
		Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	1.0	2.8	ns
t_{PHL}, t_{PLH}	Prop Delay CP to O_n (REGE = 1)	1.4	3.3	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	1.0	3.3	ns
t_{PZL}, t_{PZH}	Output Enable Time	1.0	3.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	1.0	3.8	ns
t_S	Setup Time	1.0		ns
t_H	Hold Time	0.7		ns

Note 10: This parameter is guaranteed by characterization but not tested.

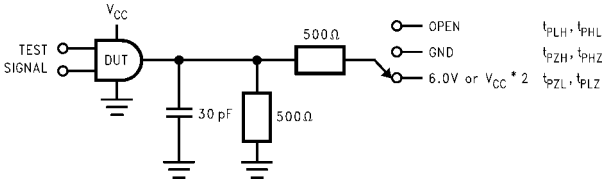
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

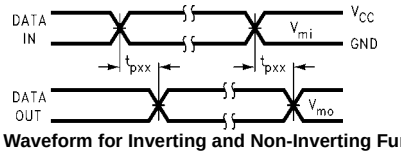


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

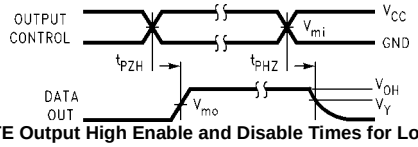


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

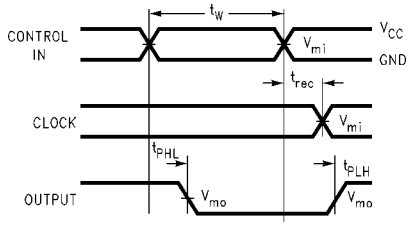


FIGURE 4. Propagation Delay, Pulse Width and t_{rec} Waveforms

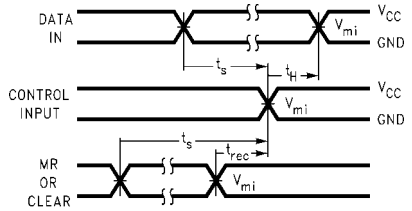
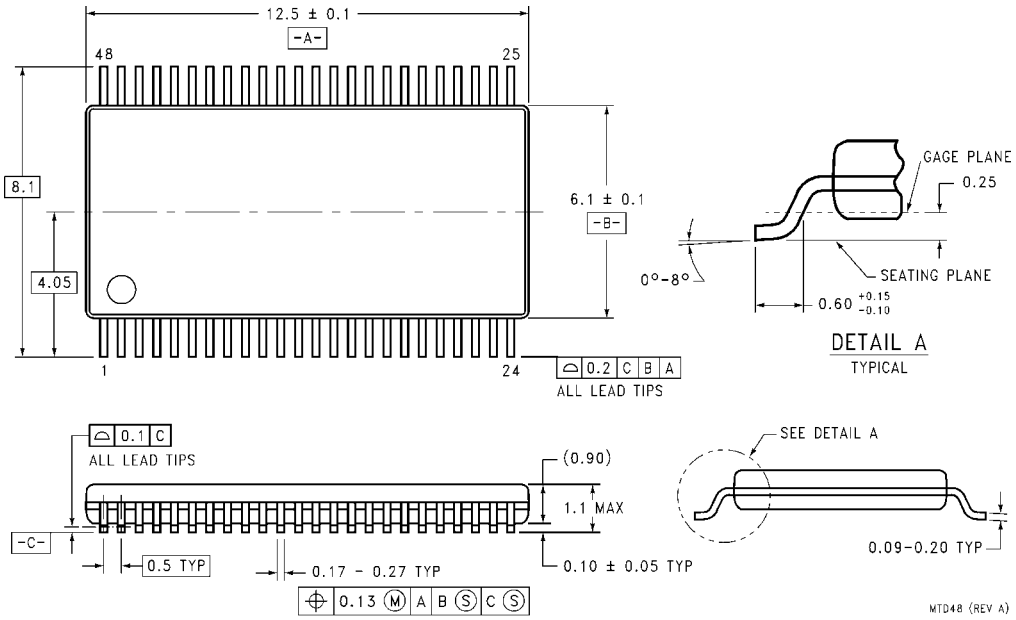


FIGURE 5. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

July 1997
Revised April 1999

74VCX16839

Low Voltage 20-Bit Selectable Register/Buffer with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16839 contains twenty non-inverting selectable buffered or registered paths. The device can be configured to operate in a registered, or flow through buffer mode by utilizing the register enable (REGE) and Clock (CP) signals. The device operates in a 20-bit word wide mode. All outputs can be placed into 3-STATE through use of the $\overline{OE}$ pin. These devices are ideally suited for buffered or registered 168 pin and 200 pin SDRAM DIMM memory modules.

The 74VCX16839 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16839 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 and PC133 DIMM module specifications
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (CP to O_n)
  - 3.2 ns max for 3.0V to 3.6V V_{CC}
  - 4.4 ns max for 2.3V to 2.7V V_{CC}
  - 8.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

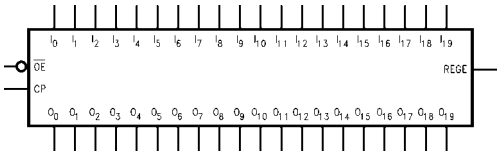
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCX16839MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

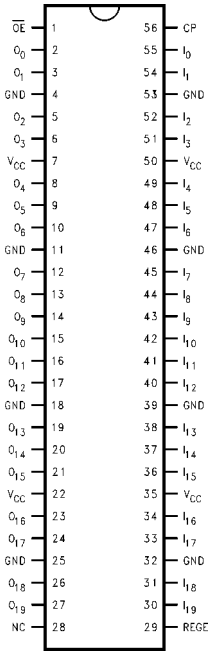
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
I_0–I_{19}	Inputs
O_0–O_{19}	Outputs
CP	Clock Pulse Input
REGE	Register Enable Input

Connection Diagram



Truth Table

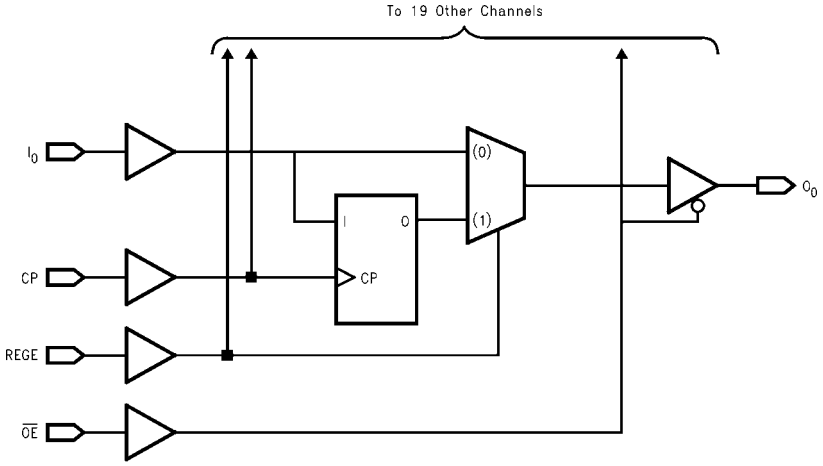
Inputs				Outputs
CP	REGE	I_n	$\overline{OE}$	O_n
↑	H	H	L	H
↑	H	L	L	L
X	L	H	L	H
X	L	L	L	L
X	X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX16839 consists of twenty selectable non-inverting buffers or registers with word wide controls. Mode functionality is selected through operation of the CP and REGE pin as shown by the truth table. When REGE is held at a logic "1" the device operates as a 20-bit register. Data is transferred from I_n to O_n on the rising edge of the CP pin. When the REGE pin is held at a logic "0" the device operates in a flow through mode and data propagates directly from the I_n to the O_n outputs. All outputs can be 3-stated by holding the $\overline{OE}$ pin at a logic "1."

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	2.3 – 2.7	V_{CC} – 0.2		V
		I_{OH} = −6 mA	2.3	2.0		V
		I_{OH} = −12 mA	2.3	1.8		V
		I_{OH} = −18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	μA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	1.65 - 2.3	V_{CC} – 0.2		V
		I_{OH} = −6 mA	1.65	1.4		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	μA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics VCX16839 (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL} t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	0.8	2.5	1.0	3.5	1.5	7.0	ns
t_{PHL} t_{PLH}	Prop Delay CP to O_n (REGE = 1)	0.8	3.2	1.0	4.4	1.5	8.8	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	0.8	4.0	1.0	5.0	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	4.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_S	Setup Time	1.0		1.0		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Extended AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 0.3V$		Units
		$C_L = 50$ pF		
		Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n (REGE = 0)	1.0	2.8	ns
t_{PHL}, t_{PLH}	Prop Delay CP to O_n (REGE = 1)	1.4	3.5	ns
t_{PHL}, t_{PLH}	Prop Delay REGE to O_n	1.0	4.3	ns
t_{PZL}, t_{PZH}	Output Enable Time	1.0	4.1	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	1.0	4.0	ns
t_S	Setup Time	1.0		ns
t_H	Hold Time	0.7		ns

Note 10: This parameter is guaranteed by characterization but not tested.

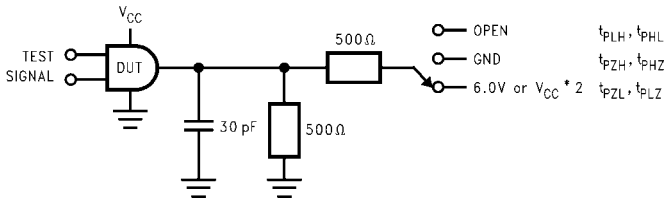
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

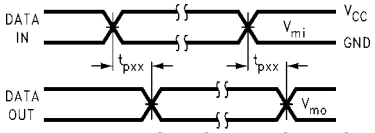


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

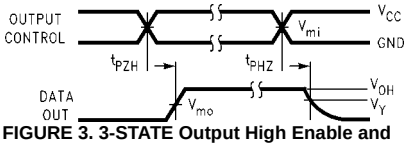


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

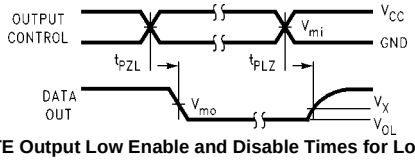


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

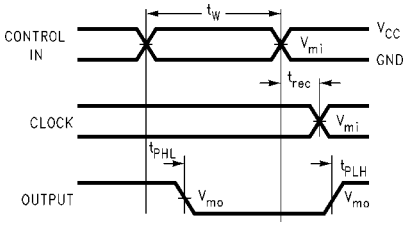


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

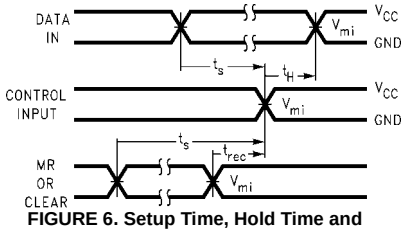
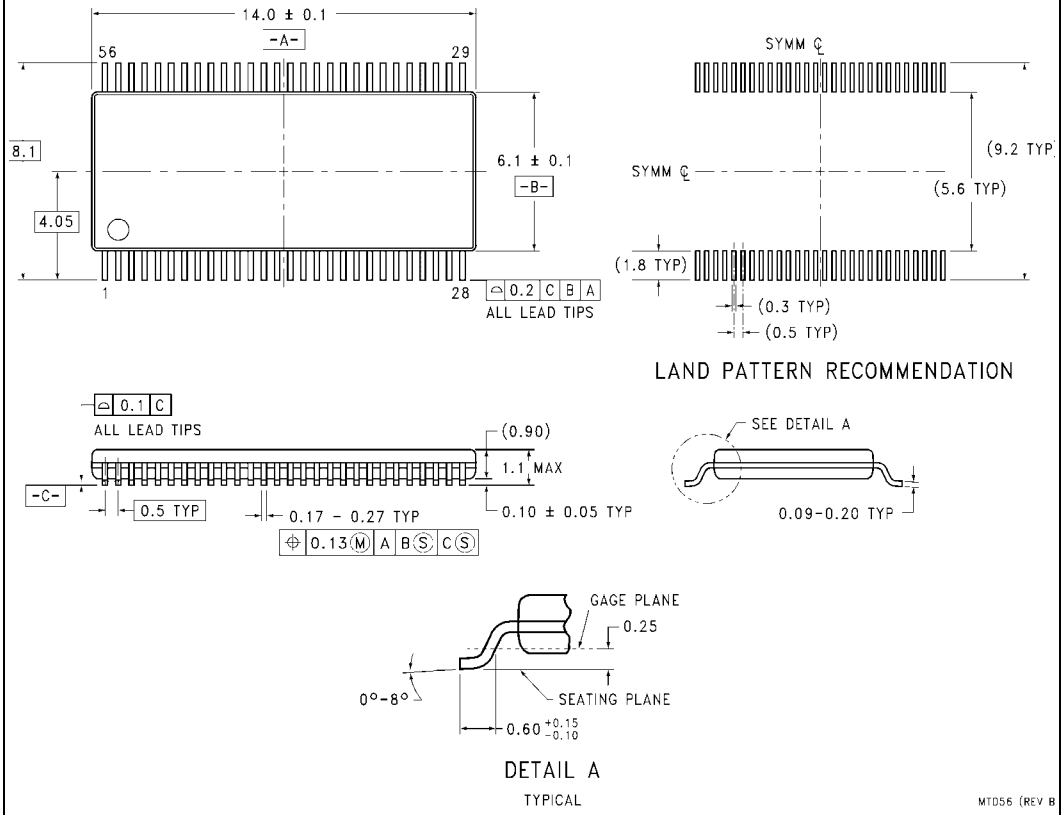


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

FAIRCHILD SEMICONDUCTOR™

March 1998
Revised April 1999

74VCX16841

Low Voltage 20-Bit Transparent Latch with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16841 contains twenty non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The 74VCX16841 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16841 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (D_n to O_n)
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 3.4 ns max for 2.3V to 2.7V V_{CC}
  - 6.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

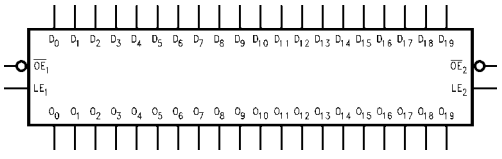
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16841MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

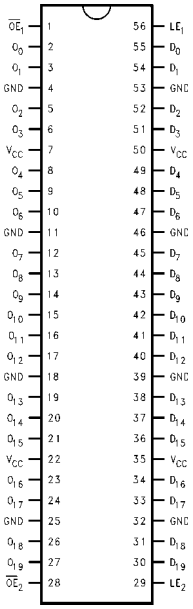
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
D_0–D_{19}	Inputs
O_0–O_{19}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	D_0–D_9	O_0–O_9
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

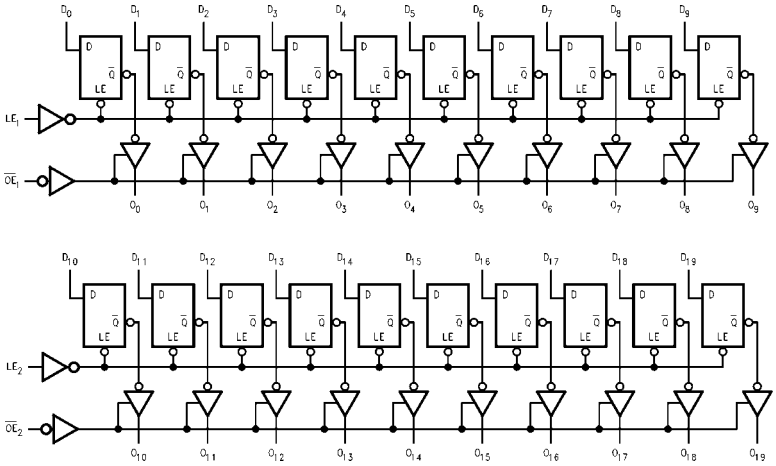
Inputs			Outputs
LE_2	$\overline{OE}_2$	D_{10}–D_{19}	O_{10}–O_{19}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCX16841 contains twenty D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 20-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the D_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change states each time its D-type input changes. When LE_n is LOW, the latches store information that was present on the D-type inputs a setup time preceding the HIGH-to-LOW transition on LE_n. The 3-STATE outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to +3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7 – 3.6	V_{CC} – 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 – 3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 18 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7 – 3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 5)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 5: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3 – 2.7	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.3	2.0		V
		I_{OH} = −12 mA	2.3	1.8		V
		I_{OH} = −18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3 – 2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	V
		I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3 – 2.7		±20	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65 - 2.3	V_{CC} − 0.2		V
		I_{OH} = −6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65 - 2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	1.65 - 2.3		±20	µA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay D_n to O_n	0.8	3.0	1.0	3.4	1.5	6.8	ns
t_{PHL}, t_{PLH}	Prop Delay LE to O_n	0.8	3.5	1.0	4.4	1.5	8.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	4.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.7	1.0	4.2	1.5	7.6	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For $C_L = 50_pF$, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

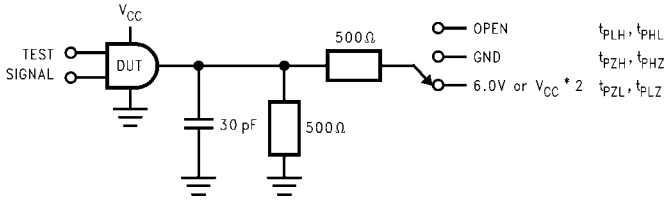
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

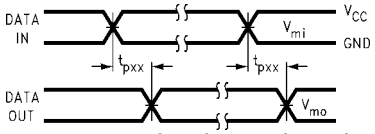


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

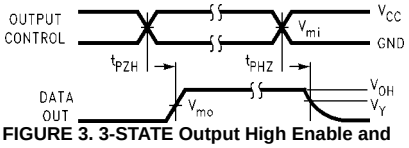


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

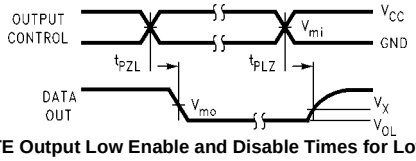


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

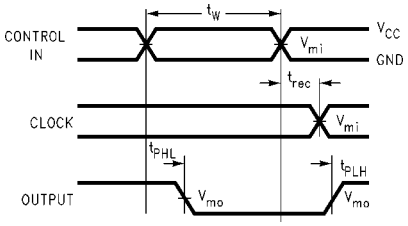


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

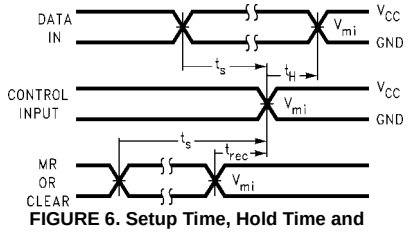
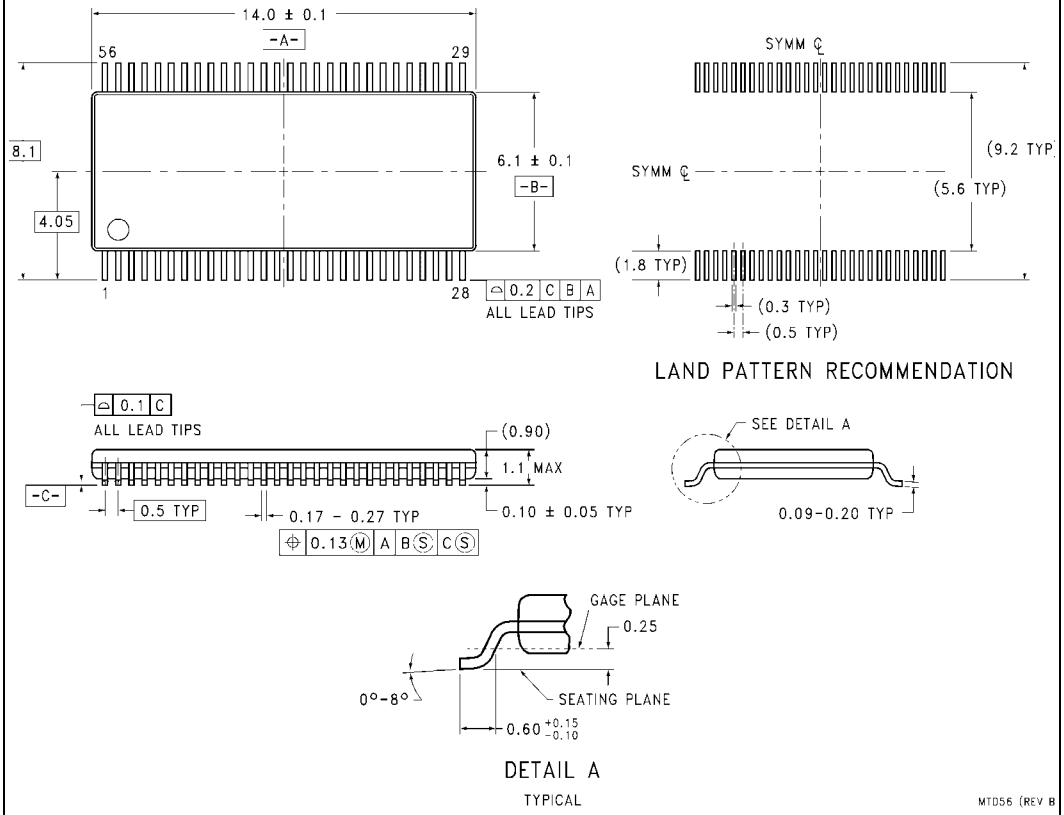


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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June 1999
Revised June 1999

74VCX2245

Low Voltage Bidirectional Transceiver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in B Outputs

General Description

The VCX2245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The T/$\overline{R}$ input determines the direction of data flow. The $\overline{OE}$ input disables both the A and B ports by placing them in a high impedance state.

The 74VCX2245 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V. The VCX2245 is also designed with 26Ω series resistance in the B Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers transmitters

The 74VCX2245 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V - 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in B Port outputs
- Power-off high impedance inputs and outputs
- Supports Live Insertion and Withdrawal (Note 1)
- t_{PD} (A to B)
  - 4.4 ns max for 3.0V to 3.6V V_{CC}
  - 5.6 ns max for 2.3V to 2.7V V_{CC}
  - 9.8 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL} B outputs):
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 200V

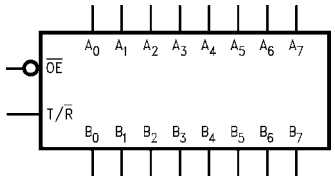
Note 1: To ensure the high impedance state during power up and power down, $\overline{OE}_n$ should be tied to V_{CC} through a pull up resistor. The minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX2245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VCX2245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

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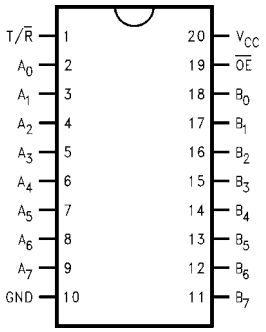
Connection Diagram



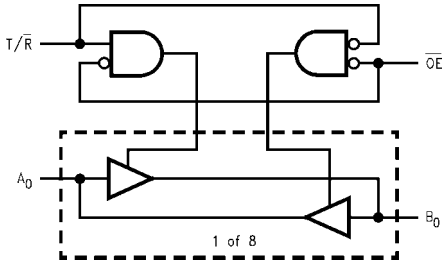
Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7 (Note 2)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Note 2: Unused bus terminals during HIGH Z State must be held HIGH or LOW.

Logic Diagram



Absolute Maximum Ratings (Note 3)

Supply Voltage (V_{CC})	–0.5V to +4.6V
DC Input Voltage (V_I)	–0.5V to +4.6V
DC Output Voltage (V_O)	
Outputs 3-STATE	–0.5V to +4.6V
Outputs Active (Note 4)	–0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	–50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	–50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current	±100 mA
Storage Temperature (T_{STG})	–65°C to +150°C

Recommended Operating Conditions (Note 5)

Power Supply Voltage (V_{CC})	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	–0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0V to 3.6V
Output Current in I_{OH}/I_{OL} - A Outputs	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Output Current in I_{OH}/I_{OL} - B Outputs	
V_{CC} = 3.0V to 3.6V	± 12 mA
V_{CC} = 2.3V to 2.7V	± 8 mA
V_{CC} = 1.65V to 2.3V	± 3 mA
Free Air Operating Temperature (T_A)	–40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA	2.7–3.6	V_{CC} – 0.2		V
	A Outputs	I_{OH} = –12 mA	2.7	2.2		
		I_{OH} = –18 mA	3.0	2.4		
		I_{OH} = –24 mA	3.0	2.2		
	HIGH Level Output Voltage	I_{OH} = –100 µA	2.7–3.6	V_{CC}–0.2		V
	B Outputs	I_{OH} = –6 mA	2.7	2.2		
		I_{OH} = –8 mA	3.0	2.4		
		I_{OH} = –12 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
	A Outputs	I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
	B Outputs	I_{OL} = 6 mA	2.7		0.4	
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12 mA	3.0		0.8	
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power Off Leakage Current	0 ≤ (V_I, V_O) ≤ 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 6)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} –0.6V	2.7–3.6		750	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC} − 0.2		V
	A Outputs	I_{OH} = −6 mA	2.3	2.0		
		I_{OH} = −12 mA	2.3	1.8		
		I_{OH} = −18 mA	2.3	1.7		
	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC}–2		V
	B Outputs	I_{OH} = −4 mA	2.3	2.0		
		I_{OH} = −6 mA	2.3	1.8		
		I_{OH} = −8mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
	A Outputs	I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
	B Outputs	I_{OL} = 6 mA	2.3		0.4	
		I_{OL} = 8 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	2.3–2.7		±20	

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–2.3	V_{CC} − 0.2		V
	A Outputs	I_{OH} = −6 mA	1.65	1.25		
	HIGH Level Output Voltage	I_{OH} = -100 µA	1.65–2.3	V_{CC}–0.2		V
	B Outputs	I_{OH} = -3 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
	A Outputs	I_{OL} = 6 mA	1.65		0.3	
	LOW Level Output Voltage	I_{OL} = 100µA	1.65–2.3		0.2	V
	B Outputs	I_{OL} = 3 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65-2.3		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 8)	1.65–2.3		±20	

Note 8: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 9)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay, A to B	0.6	4.4	0.8	5.6	1.5	9.8	ns
t_{PHL} t_{PLH}	Propagation Delay, B to A	0.6	3.5	0.8	4.2	1.5	8.4	ns
t_{PZL} t_{PZH}	Output Enable Time, A to B	0.6	5.0	0.8	6.6	1.5	9.8	ns
t_{PZL} t_{PZH}	Output Enable Time, B to A	0.6	4.5	0.8	5.6	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time, A to B	0.6	4.2	0.8	4.7	1.5	8.5	ns
t_{PLZ} t_{PHZ}	Output Disable Time, B to A	0.6	3.6	0.8	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 10)		0.5		0.5		0.75	ns

Note 9: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.3	V
			2.5	0.7	
			3.3	1.0	
	Quiet Output Dynamic Peak V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.2	V
			2.5	0.45	
			3.3	0.65	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.3	V
			2.5	–0.7	
			3.3	–1.0	
	Quiet Output Dynamic Valley, V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.2	V
			2.5	–0.45	
			3.3	–0.65	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.3	V
			2.5	1.7	
			3.3	2.0	
	Quiet Output Dynamic Valley V_{OH}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	2.0	
			3.3	2.5	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	6	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

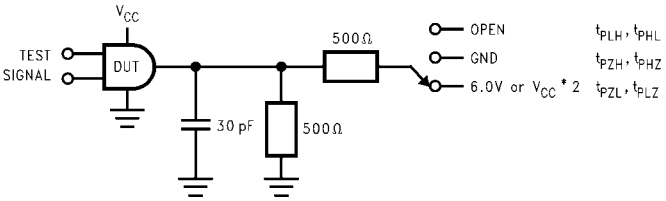


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5V ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

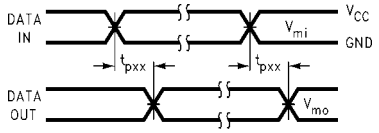


FIGURE 2. Waveform for Inverting and Non-inverting Functions

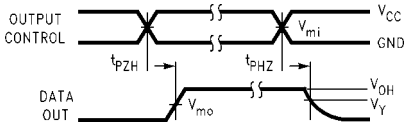


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

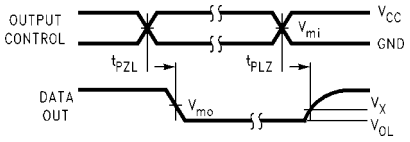
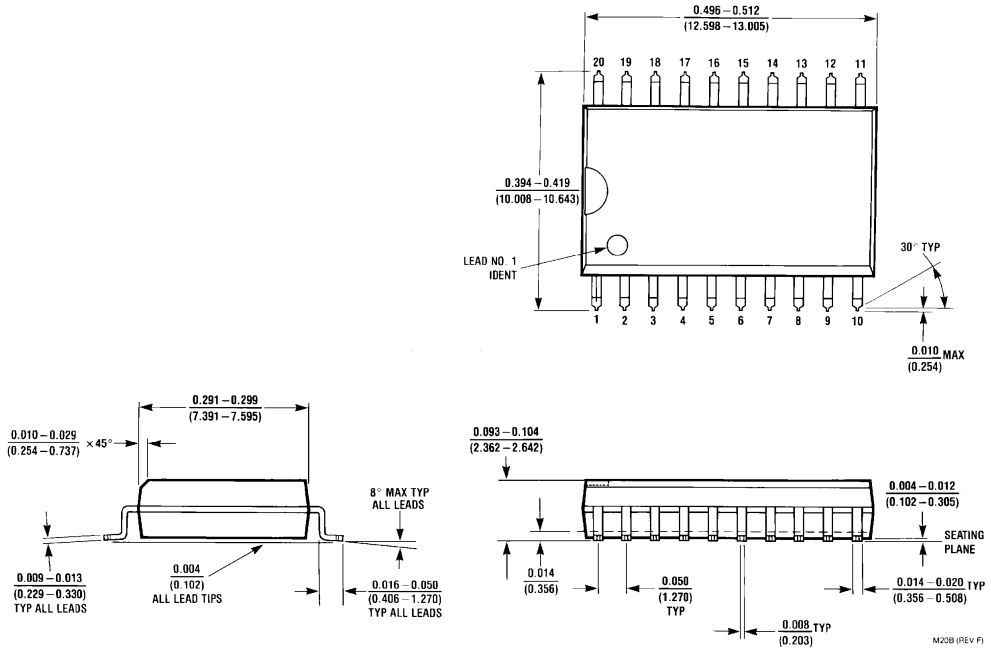


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

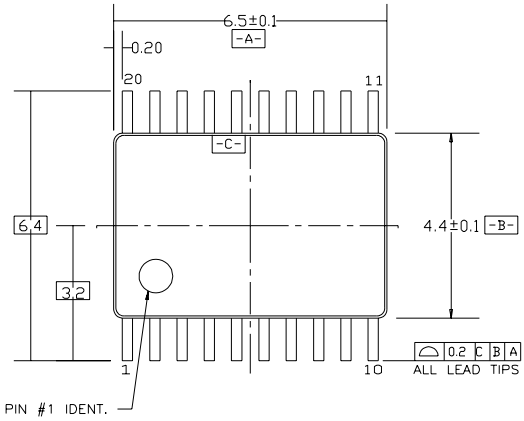
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

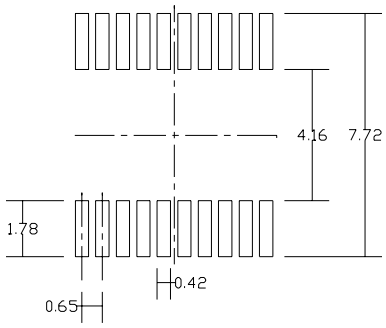
Physical Dimensions inches (millimeters) unless otherwise noted



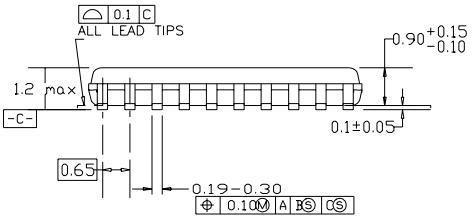
20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

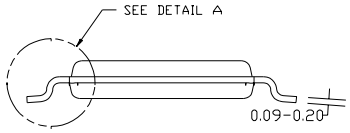
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



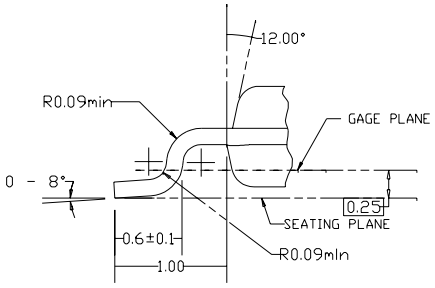


LAND PATTERN RECOMMENDATION





DIMENSIONS ARE IN MILLIMETERS



DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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FAIRCHILD SEMICONDUCTOR™

June 1999
Revised July 1999

74VCX245
Low Voltage Bidirectional Transceiver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The T/$\overline{R}$ input determines the direction of data flow. The $\overline{OE}$ input disables both the A and B ports by placing them in a high impedance state.

The 74VCX245 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX245 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V-3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- Power-off high impedance inputs and outputs
- Supports Live Insertion and Withdrawal (Note 1)
- t_{PD}
  - 3.5 ns max for 3.0V to 3.6V V_{CC}
  - 4.2 nx max for 2.3V to 2.7V V_{CC}
  - 8.4 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

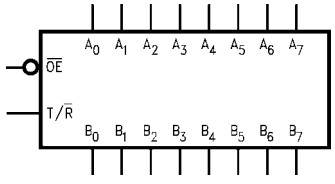
Note 1: To ensure the high impedance state during power up and power down, $\overline{OE}_n$ should be tied to V_{CC} through a pull up resistor. The minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VCX245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

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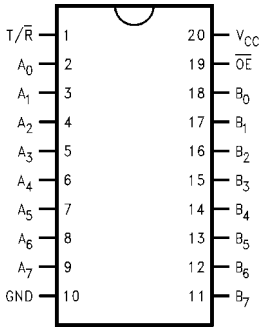
Connection Diagram



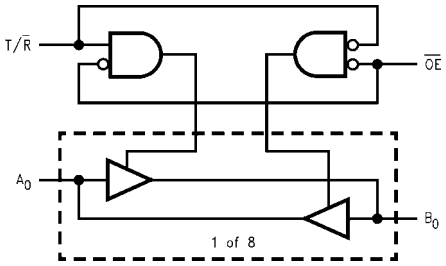
Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7 (Note 2)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Note 2: Unused bus terminals during HIGH Z State must be held HIGH or LOW.

Logic Diagram



Absolute Maximum Ratings (Note 3)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
DC Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 4)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current	±100 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 5)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power Off Leakage Current	0 ≤ (V_I, V_O) ≤ 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 6)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	µA
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 7)	2.3–2.7		±20	

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65–2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65–2.3		0.2	V
		$I_{OL} = 6$mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 8)	1.65–2.3		±20	

Note 8: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 9)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay A_n to B_n or B_n to A_n	0.6	3.5	0.8	4.2	1.5	8.4	ns
t_{PZL} t_{PZH}	Output Enable Time	0.6	4.5	0.8	5.6	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time	0.6	3.6	0.8	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 10)		0.5		0.5		0.75	ns

Note 9: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.3	
			2.5	0.7	V
			3.3	1.0	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.3	
			2.5	–0.7	V
			3.3	–1.0	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.3	
			2.5	1.7	V
			3.3	2.0	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	6	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

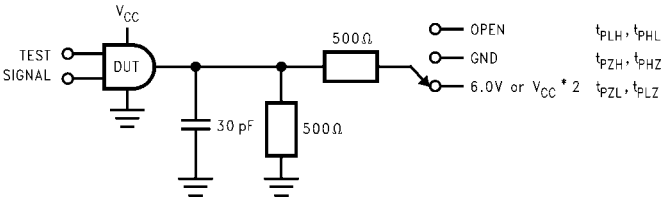


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5V ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

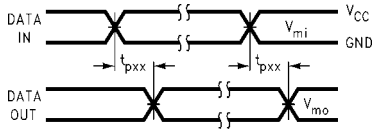


FIGURE 2. Waveform for Inverting and Non-inverting Functions

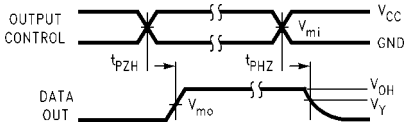


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

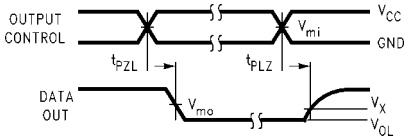
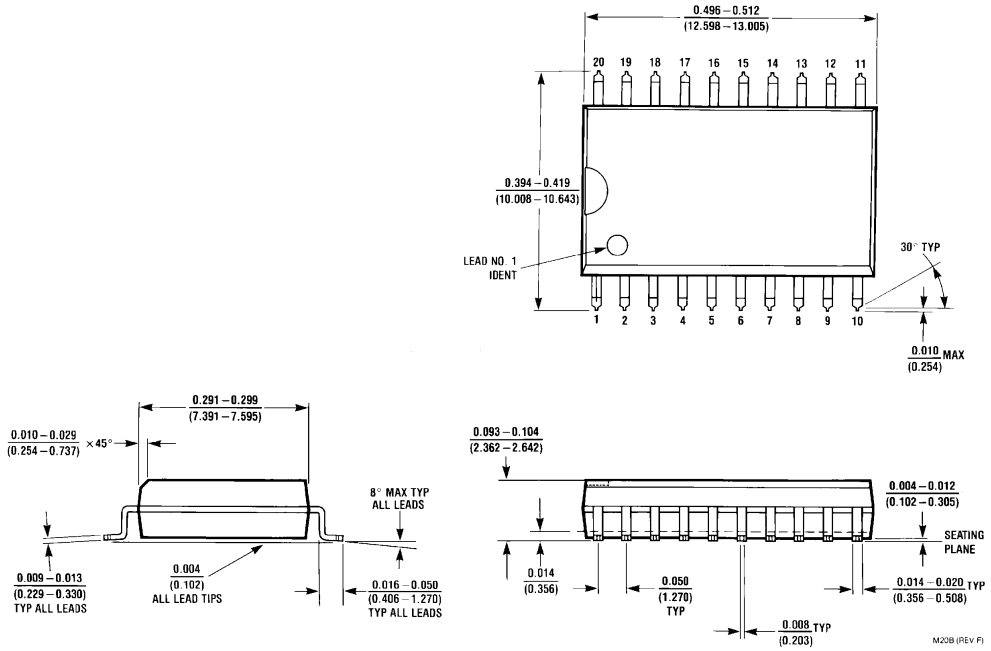


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

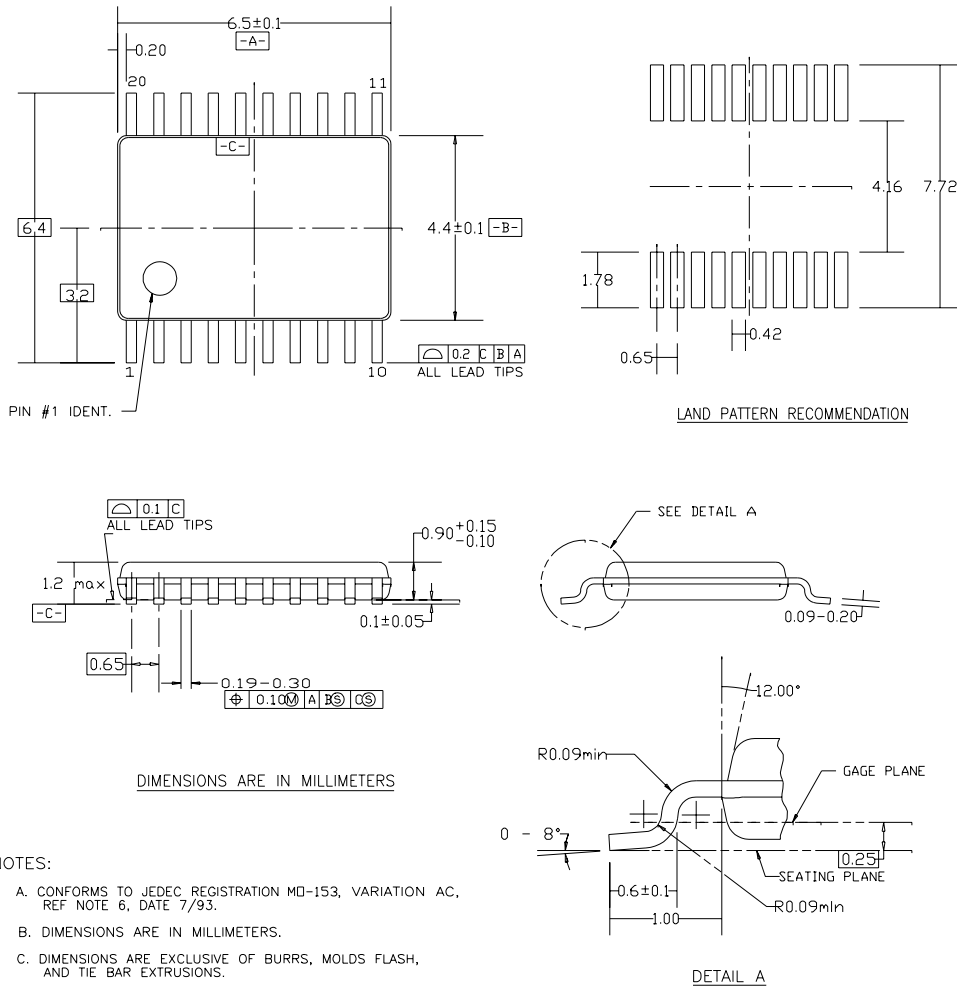
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised July 1999

74VCX32
Low Voltage Quad 2-Input OR Gate with 3.6V Tolerant Inputs and Outputs

General Description

The VCX32 contains four 2-input OR gates. This product is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The VCX32 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

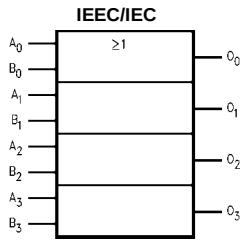
- 1.65V-3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.8 ns max for 3.0V to 3.6V V_{CC}
  - 3.7 ns max for 2.3V to 2.7V V_{CC}
  - 7.4 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

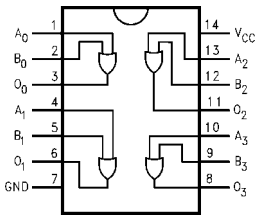
Order Number	Package Number	Package Description
74VCX32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VCX32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to 4.6V
DC Output Voltage (V_O)	
HIGH or LOW State (Note 2)	−0.5V to V_{CC} + 0.5V
V_{CC} = 0V	−0.5V to +4.6V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
HIGH or LOW State	0V to V_{CC}
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OFF}	Power Off Leakage Current	0 ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ V_I ≤ 3.6V	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

DC Electrical Characteristics ($2.3V \leq V_{CC} \leq 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.3	2.0		
		$I_{OH} = -12$ mA	2.3	1.8		
		$I_{OH} = -18$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 12$ mA	2.3		0.4	
		$I_{OL} = 18$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.3–2.7		±5.0	µA
I_{OFF}	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \leq V_I$ 3.6V	2.3–2.7		±20	

DC Electrical Characteristics ($1.65V \leq V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65–2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65–2.3		0.2	V
		$I_{OL} = 6$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	1.65–2.3		±5.0	µA
I_{OFF}	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \leq V_I \leq 3.6V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30pF$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}	Propagation Delay	0.6	2.8	0.8	3.7	1.0	7.4	ns
t_{PLH}								
t_{OSHL}	Output to Output		0.5		0.5		0.75	ns
t_{OSLH}	Skew (Note 5)							

Note 4: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C Typical	Unit
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	T_A = +25°C Typical	Units
C_{IN}	Input Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

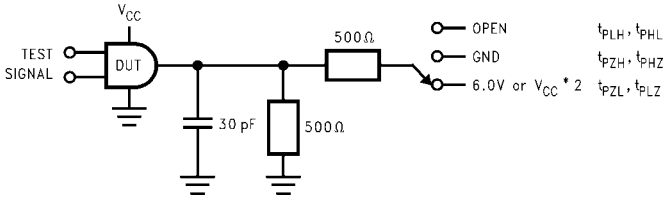


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open

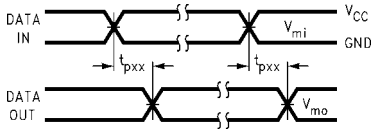
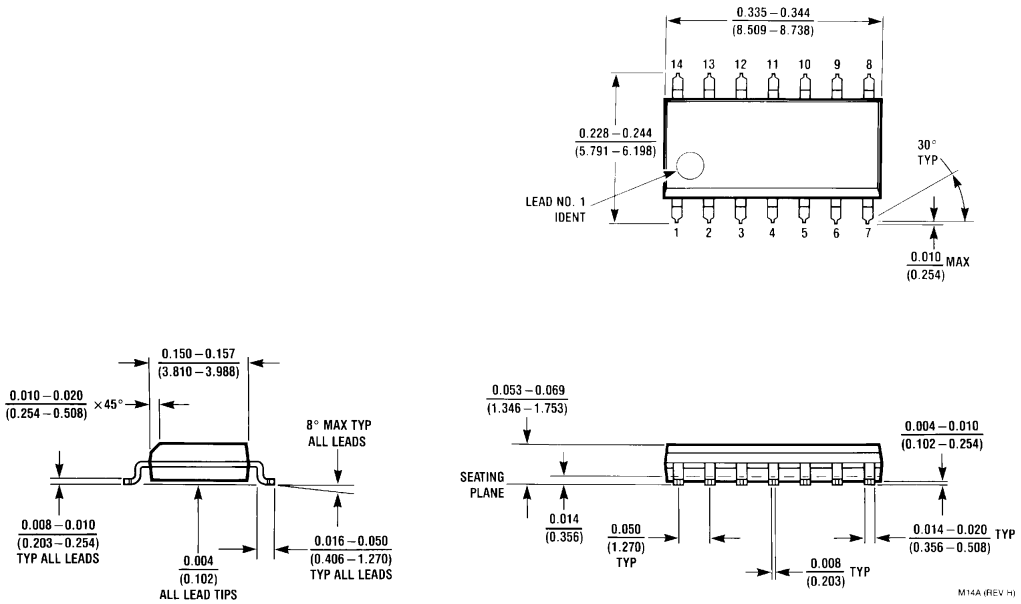


FIGURE 2. Waveform for Inverting and Non-inverting Functions

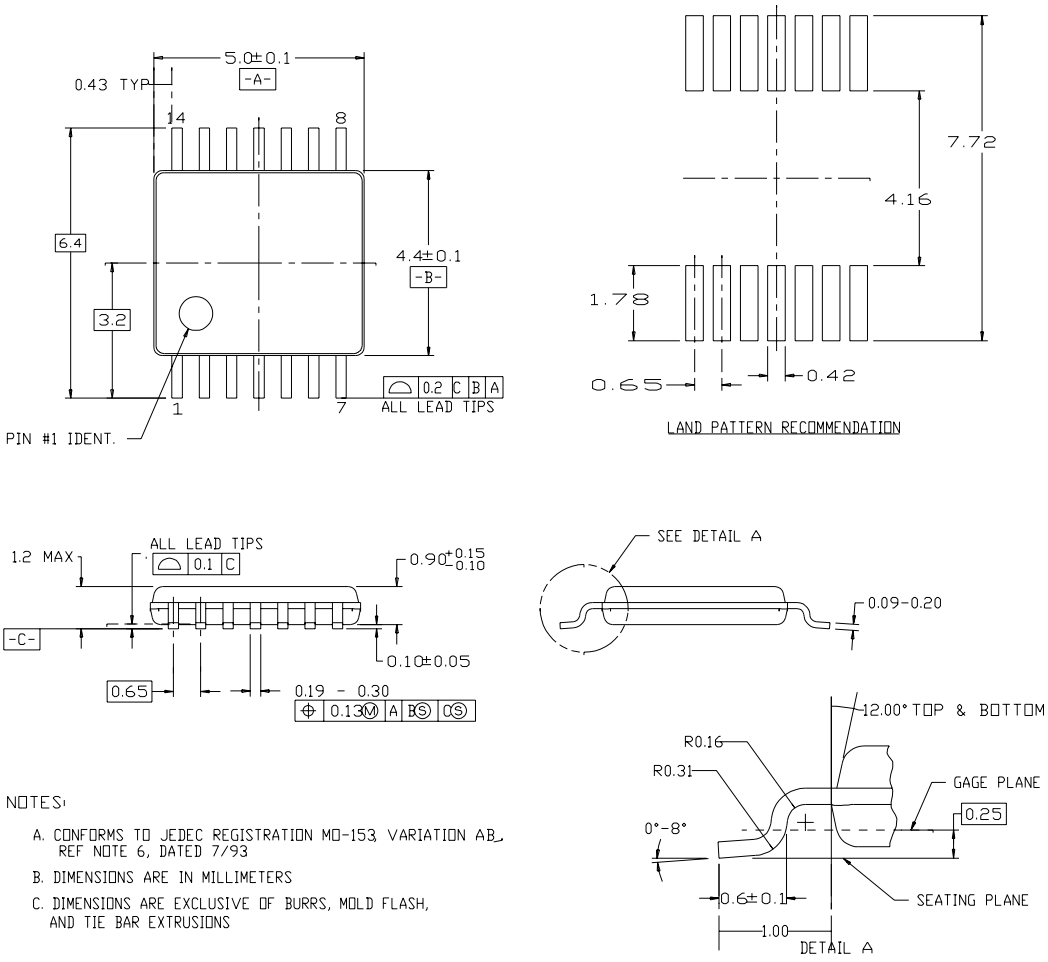
Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1999
Revised July 1999

74VCX38

Low Voltage Quad 2-Input NAND Gate with Open Drain Outputs and 3.6V Tolerant Inputs and Outputs

General Description

The VCX38 contains four 2-input NAND gates with open drain outputs. This product is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The VCX38 is fabricated with advanced CMOS technology to achieve high-speed operation while maintaining CMOS low power dissipation.

Features

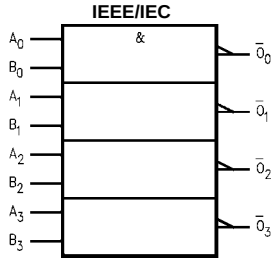
- 1.65V-3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 2.8 ns max for 3.0V to 3.6V V_{CC}
  - 3.7 ns max or 2.3V to 2.7V V_{CC}
  - 6.7 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

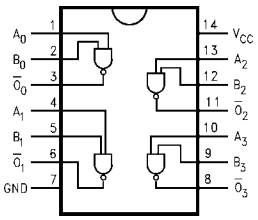
Order Number	Package Number	Package Description
74VCX38M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VCX38MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O) (Note 2)	−0.5V to +4.6V
DC Input Diode Current (I_{IK})	
$V_I < 0V$	−50 mA
DC Output Diode Current (I_{OK})	
$V_O < 0V$	−50 mA
DC Output Source/Sink Current (I_{OL})	+50 mA
DC V_{CC} or Ground Current per	±100 mA
Supply Pin (I_{CC} or Ground)	
Storage Temperature Range (T_{stg})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	0V to V_{CC}
Output Current in I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{in} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	μA
I_{OFF}	Power-Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7–3.6		20	μA
		$V_{CC} \leq V_I \leq 3.6V$	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7–3.6		750	μA

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.8	V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le V_I \le 3.6V$	2.3–2.7		±20	

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \le V_I \le 3.6V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, C_L = 30 pF, R_L = 500Ω						Units
		V_{CC} = 3.3V ±0.3V		V_{CC} = 2.5V ±0.2V		V_{CC} = 1.8V ±0.15V		
		Min	Max	Min	Max	Min	Max	
t_{PZL} t_{PLZ}	Propagation Delay	0.6	2.8	0.8	3.7	1.0	6.7	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 5)		0.5		0.5		0.75	ns

Note 4: For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = +25°C Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 30 pF, $V_{IH} = V_{CC}$, V_{IL} = 0V	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	

Capacitance

Symbol	Parameter	Conditions	T_A +25°C Typical	Units
C_{IN}	Input Capacitance	V_I = 0v OR V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

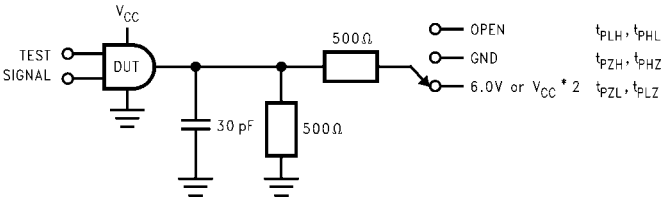


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} × 2 at V_{CC} = 2.5V ± 0.2V; 1.8V

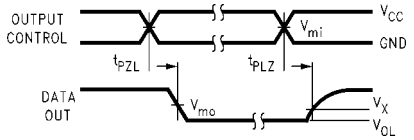
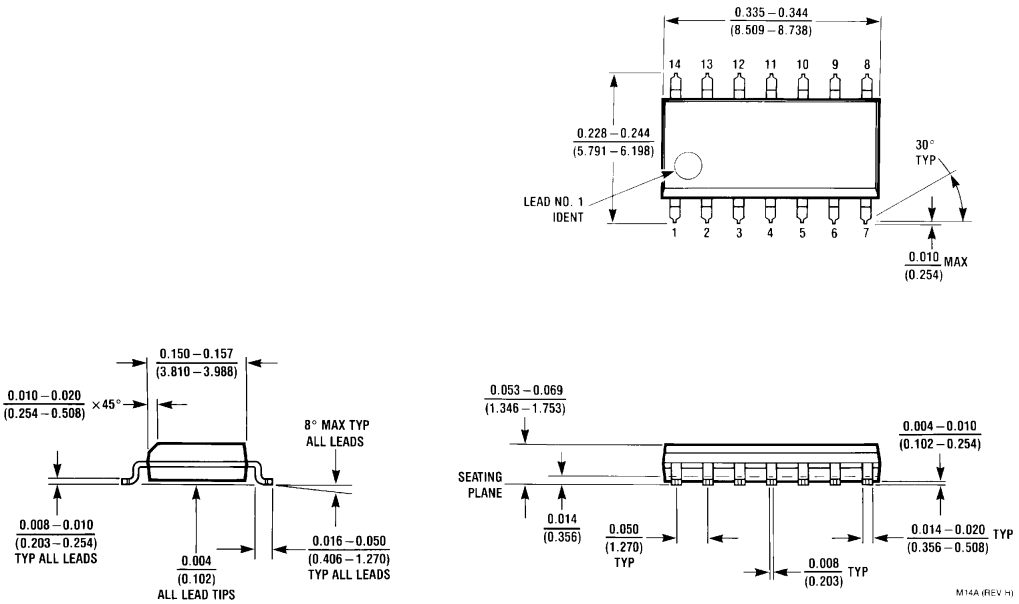


FIGURE 2. Waveform for Open Drain, Inverting and Non-inverting Functions

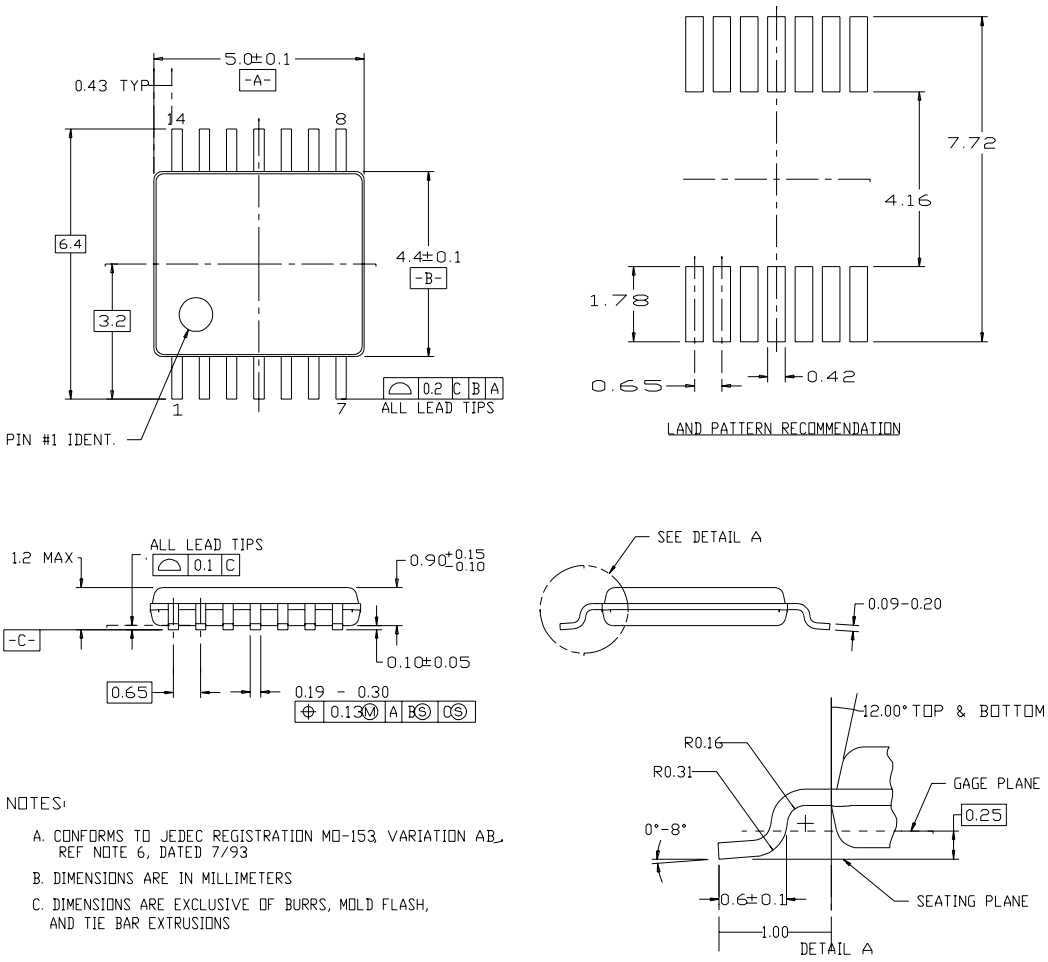
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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July 1999
Revised July 1999

74VCX86
Low Voltage Quad 2-Input Exclusive-OR Gate with 3.6V Tolerant Inputs and Outputs

General Description

The VCX86 contains four 2-input exclusive OR gates. This product is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V

The 74VCX86 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

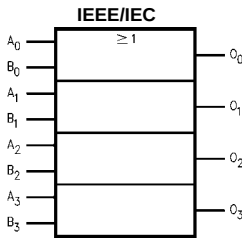
- 1.65V-3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 3.9 ns max for 2.3V to 2.7V V_{CC}
  - 7.8 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 ma @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

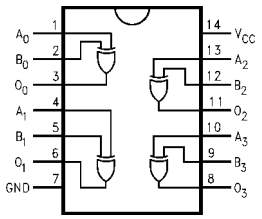
Order Number	Package Number	Package Description
74VCX86M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VCX86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
HIGH or LOW State (Note 2)	−0.5V to V_{CC} +0.5V
V_{CC} = 0V	−0.5V to +4.6V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per	±100 mA
Supply Pin (I_{CC} or Ground)	
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
HIGH or LOW State	0V to V_{CC}
Output Current in I_{OH}/i_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		$V_{CC} \leq V_I \leq 3.6V$	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.3	2.0		
		I_{OH} = −12 mA	2.3	1.8		
		I_{OH} = −18 mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA
		$V_{CC} \le V_I \le 3.6V$	2.3–2.7		±20	

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–2.3	V_{CC} − 0.2		V
		I_{OH} = −6 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
I_{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA
		$V_{CC} \le V_I \le 3.6V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30pF$, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay	0.6	3.0	0.8	3.9	1.0	7.8	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 5)		0.5		0.5		0.75	ns

Note 4: For C_L = 50 pf, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	C_L = 30 pF, V_{IH} = V_{CC}, V_{IL} = 0V	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	T_A = +25°C Typical	Units
C_{IN}	Input Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{CC}, V_{CC} = 1.8V, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{CC}, f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

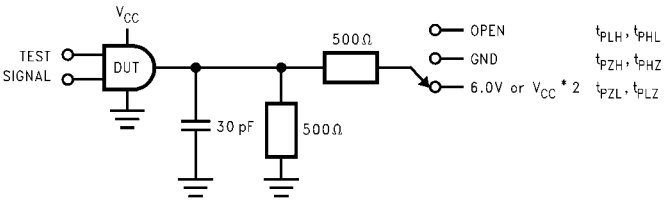


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH},t_{PHL}	Open

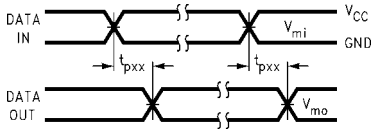
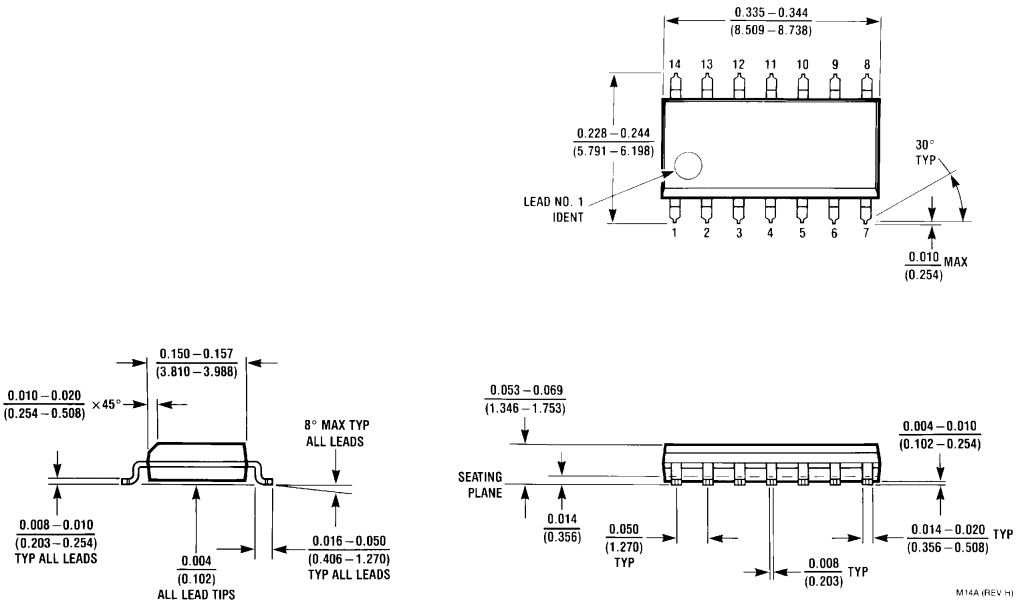


FIGURE 2. Waveform for Inverting and Non-inverting Functions

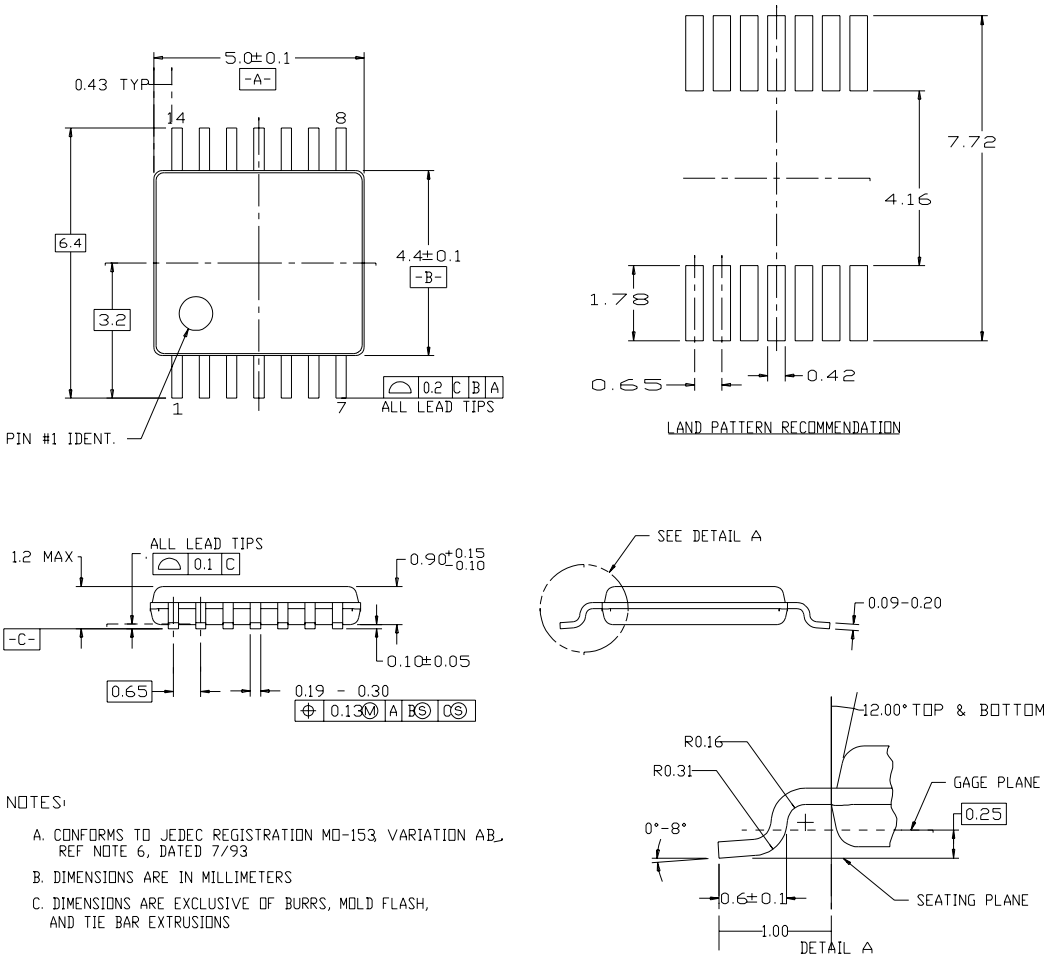
Symbol	V_{CC}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2

Physical Dimensions inches (millimeters) unless otherwise noted



14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1999
Revised October 1999

74VCXF162835
Low Voltage 18-Bit Universal Bus Driver with 3.6V Tolerant Outputs and 26Ω Series Resistors in Outputs

General Description

The VCXF162835 low voltage 18-bit universal bus driver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched and clocked modes.

Data flow is controlled by output-enable ($\overline{OE}$), latch-enable (LE), and clock (CLK) inputs. The device operates in Transparent Mode when LE is held HIGH. The device operates in clocked mode when LE is LOW and CLK is toggled. Data transfers from the Inputs (I_n) to Outputs (O_n) on a Positive Edge Transition of the Clock. When $\overline{OE}$ is LOW, the output data is enabled. When $\overline{OE}$ is HIGH the output port is in a high impedance state.

The VCXF162835 is designed with 26Ω series resistors in the outputs. This design reduces noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCXF162835 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCXF162835 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

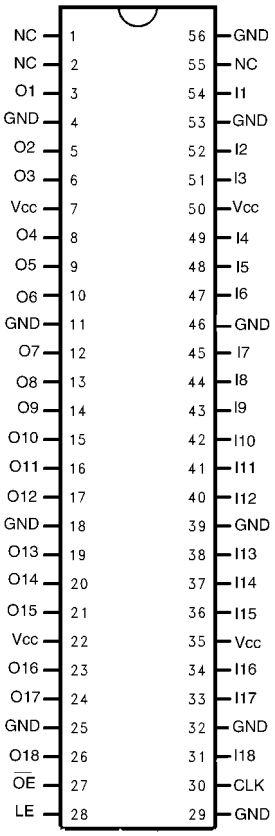
- Compatible with PC133 DIMM module specifications
- 1.65V–3.6V V_{CC} specifications provided
- 3.6V tolerant outputs
- 26Ω series resistors in outputs
- t_{PD} (CP to O_n)
  - 3.2 ns max for 3.0V to 3.6V V_{CC}
  - 4.1 ns max for 2.3V to 2.7V V_{CC}
  - 7.4 ns max for 1.65V to 1.95V V_{CC}
- Power-down high impedance outputs
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

Ordering Code:

Order Number	Package Number	Package Description
74VCXF162835MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TUBES]
74VCXF162835MTX (Note 1)	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

Note 1: Use this Order Number to receive devices in Tape and Reel.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable Input
CP	Clock Input
I_1 - I_{18}	Data Inputs
O_1 - O_{18}	3-STATE Outputs

Function Table

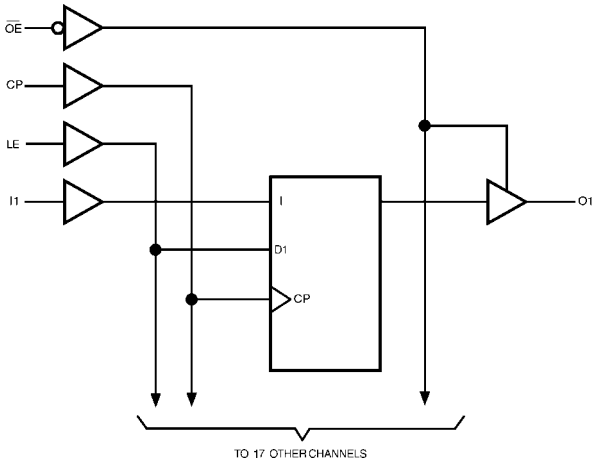
Inputs				Outputs
$\overline{OE}$	LE	CP	I_n	O_n
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	↑	L	L
L	L	↑	H	H
L	L	H	X	Io (Note 2)
L	L	L	X	Io (Note 3)

H = HIGH Voltage Level
L = LOW Level Voltage
X = Immaterial (HIGH or LOW, Inputs may not float)
Z = High Impedance

Note 2: Output level before the indicated steady-state input conditions were established provided that CP was HIGH before LE went LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Logic Diagram



Absolute Maximum Ratings (Note 4)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 5)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK})	
V_I < −0.5V	−50 mA
V_I > V_{CC} + 0.5V (Note 6)	+50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 4: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Inputs do not have over-voltage tolerance.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		
		I_{OH} = −8 mA	3.0	2.4		
		I_{OH} = −12 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 6mA	2.7		0.4	
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12mA	3.0		0.8	
I_I	Input Leakage Current	$V_I = V_{CC}$ or GND	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V; $V_I = V_{IH}$ or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power Off Leakage Current	0V ≤ (V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_O) ≤ 3.6V (Note 8)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC}$ − 0.6V	2.7–3.6		750	µA

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	2.3	2.0		
		$I_{OH} = -6$ mA	2.3	1.8		
		$I_{OH} = -8$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 6$ mA	2.3		0.4	
		$I_{OL} = 8$ mA	2.3		0.6	
I_I	Input Leakage Current	$V_I = V_{CC}$ or GND	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \le (V_O) \le 3.6V$ (Note 9)	2.3–2.7		±20	

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
		$I_{OL} = 3$ mA	1.65		0.3	
I_I	Input Leakage Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_O) \le 3.6V$ (Note 10)	1.65 - 2.3		±20	

Note 10: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 11)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8 \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Propagation Delay Bus to Bus	0.6	3.1	0.8	4.0	1.5	7.2	ns
t_{PHL}, t_{PLH}	Propagation Delay Clock to Bus	1.0	3.2	1.5	4.1	2.0	7.4	ns
t_{PHL}, t_{PLH}	Propagation Delay LE to Bus	0.6	3.7	0.8	4.7	1.5	8.5	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.6	4.3	0.8	5.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.6	4.2	0.8	4.7	1.5	7.9	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	0.7		0.7		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 12)		0.5		0.5		0.75	ns

Note 11: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

AC Electrical Characteristics Over Load (Note 13)

Symbol	Parameter	$T_A = -0°C$ to $+85°C$, $R_L = 500\Omega$ $V_{CC} = 3.3V \pm 03V$		Units
		$C_L = 50$ pF		
		Min	Max	
t_{PHL}, t_{PLH}	Prop Delay Bus to Bus	1.0	3.4	ns
t_{PHL}, t_{PLH}	Prop Delay Clock to Bus	1.4	3.5	ns
t_{PHL}, t_{PLH}	Prop Delay LE to Bus	1.0	4.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	1.0	4.6	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	1.0	4.5	ns
t_S	Setup Time	1.0		ns
t_H	Hold Time	0.6		ns

Note 13: Characterized only.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.40	
			3.3	0.55	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.25	V
			2.5	−0.40	
			3.3	−0.55	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.35	V
			2.5	1.80	
			3.3	2.30	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V, or 3.3V,	3.5	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	5.5	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	13	pF

I_{OUT} - V_{OUT} Characteristics

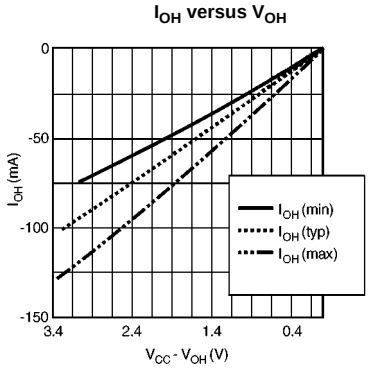


FIGURE 1. Characteristics for Output - Pull Up Drive

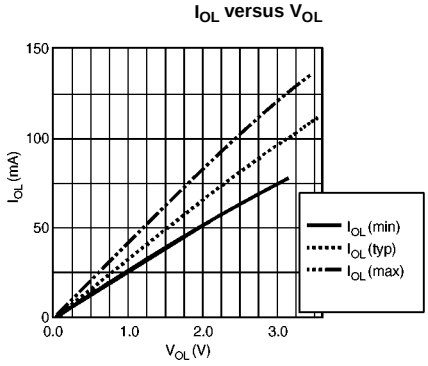


FIGURE 2. Characteristics for Output - Pull Down Driver

AC Loading and Waveforms

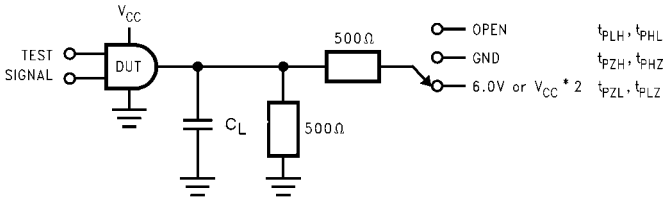


FIGURE 3. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V to ± 0.15V
t_{PZH}, t_{PHZ}	GND

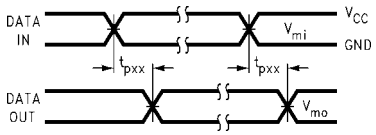


FIGURE 4. Waveform for Inverting and Non-inverting Functions
$t_r = t_f \leq$ 2.0ns, 10% to 90%

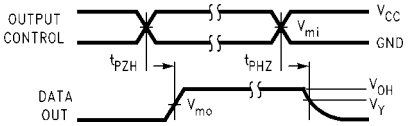


FIGURE 5. 3-STATE Output High Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

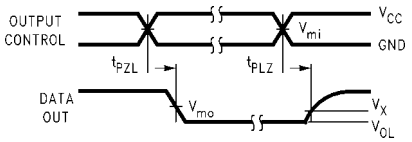
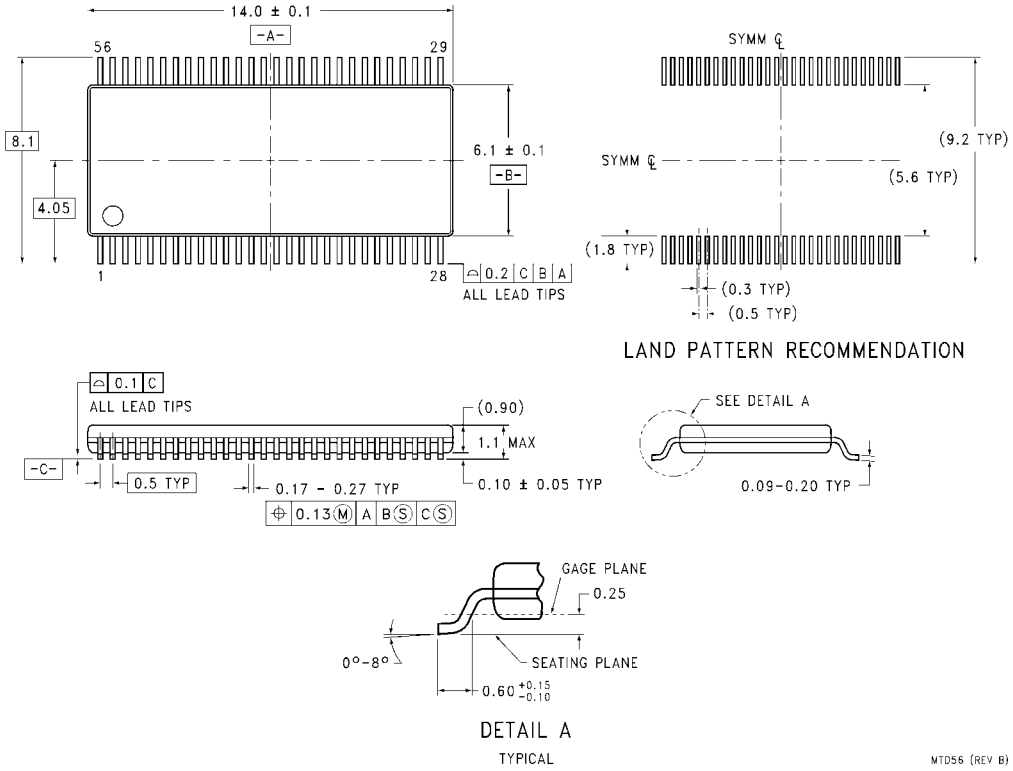


FIGURE 6. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic
$t_r = t_f \leq$ 2.0ns, 10% to 90%

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8 ± 0.15V**
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74VCXH162240
Low Voltage 16-Bit Inverting Buffer/Line Driver with Bushold and 26Ω Series Resistors in Outputs

General Description

The VCXH162240 contains sixteen inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The VCXH162240 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH162240 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCXH162240 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output capability up to 3.6V.

The 74VCXH162240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

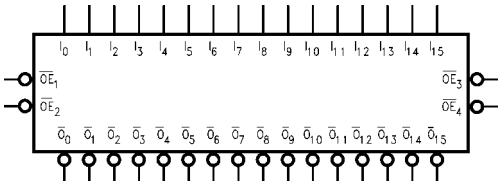
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- 26Ω series resistors in outputs
- t_{PD}
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 3.8 ns max for 2.3V to 2.7V V_{CC}
  - 7.6 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCXH162240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JECED MO-153, 6.1mm Wide [TUBES]
74VCXH162240MTX (Note 1)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JECED MO-153, 6.1mm Wide [TAPE and REEL]

Note 1: Use this Order Number to receive devices in Tape and Reel.

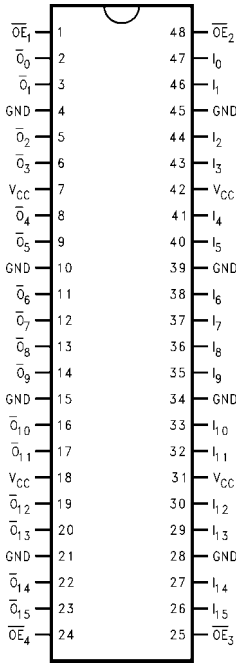
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Bushold Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

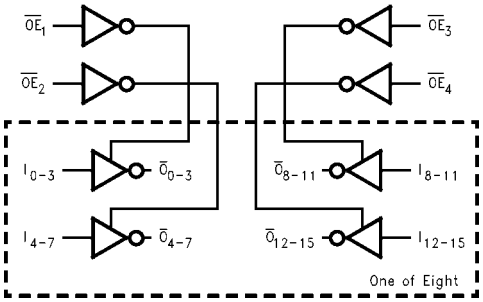
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCXH162240 contains sixteen inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
			I_{OH} = −6 mA	2.7	2.2		V
			I_{OH} = −8 mA	3.0	2.4		V
			I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7 – 3.6		0.2	V
			I_{OL} = 6 mA	2.7		0.4	V
			I_{OL} = 8 mA	3.0		0.55	V
			I_{OL} = 12 mA	3.0		0.80	V
I_I	Input Leakage Current	Control Pins	$0 \leq V_I \leq 3.6V$	2.7 – 3.6		±5.0	µA
		Data Pins	$0 \leq V_I \leq V_{CC}$	2.7 – 3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current		V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 5)	3.6	450		µA
	Current to Change State		(Note 6)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \leq (V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7 – 3.6		20	µA
			$V_{CC} \leq (V_O) \leq 3.6V$ (Note 7)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		$V_{IH} = V_{CC}$ −0.6V	2.7 – 3.6		750	µA

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	2.3 – 2.7	V_{CC} − 0.2		V
			I_{OH} = −4 mA	2.3	2.0		V
			I_{OH} = −6 mA	2.3	1.8		V
			I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	2.3 – 2.7		0.2	V
			I_{OL} = 6 mA	2.3		0.4	V
			I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3 – 2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.7V	2.3	45		μA
	Drive Hold Current		V_{IN} = 1.6V	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 8)	2.7	300		μA
	Current to Change State		(Note 9)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 10)	2.3 – 2.7		±20	μA

Note 8: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 9: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 10: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	1.65 - 2.3	V_{CC} − 0.2		V
			I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	1.65 - 2.3		0.2	V
			I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65 - 2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.57V	1.65	25		μA
	Drive Hold Current		V_{IN} = 1.07V	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 11)	1.95	200		μA
	Current to Change State		(Note 12)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 13)	1.65 - 2.3		±20	μA

Note 11: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 12: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 13: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 14)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.3	1.0	3.8	1.5	7.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	5.1	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.6	1.0	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 15)		0.5		0.5		0.75	ns

Note 14: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

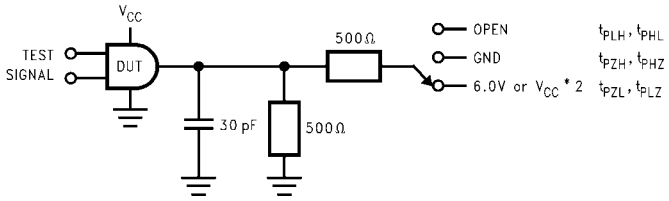
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC}	$T_A = +25°C$	Units
			(V)	Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	
			2.5	–0.25	V
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

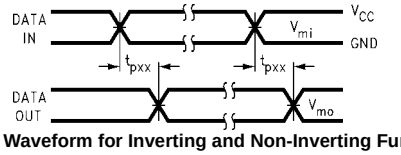


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

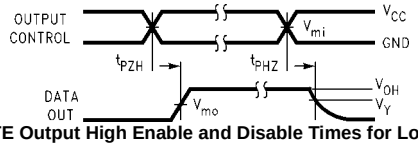


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

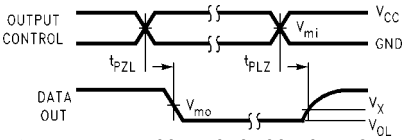
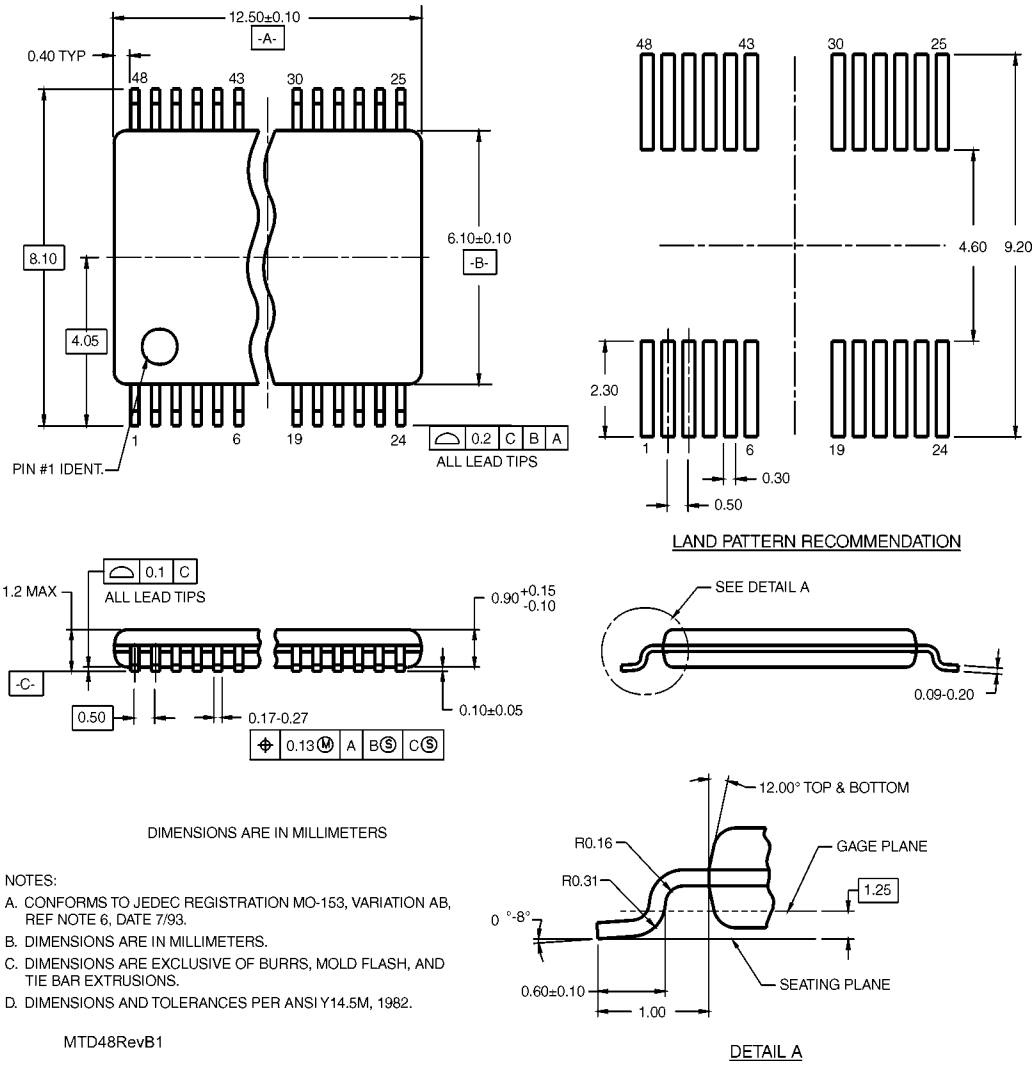


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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January 2000
Revised January 2000

74VCXH162244
Low Voltage 16-Bit Buffer/Line Driver with Bushold and 26Ω Series Resistor in Outputs

General Description

The VCXH162244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation. .

The VCXH162244 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level

The 74VCXH162244 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCXH162244 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output capability up to 3.6V.

The 74VCXH162244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

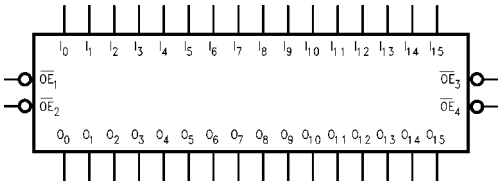
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- 26Ω series resistors in outputs
- t_{PD}
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 3.8 ns max for 2.3V to 2.7V V_{CC}
  - 7.6 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description
74VCXH162244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TUBES]
74VCXH162244MTX (Note 1)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

Note 1: Use this Order Number to receive devices in Tape and Reel.

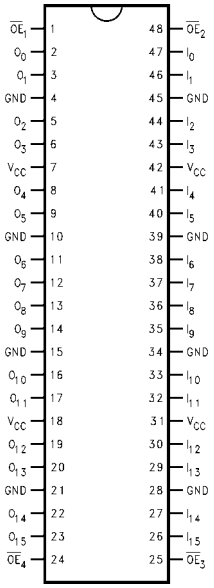
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Bushold Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	O_4–O_7
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

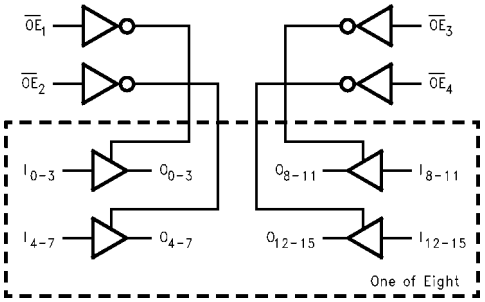
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	O_{12}–O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCXH162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
			I_{OH} = −6 mA	2.7	2.2		V
			I_{OH} = −8 mA	3.0	2.4		V
			I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7–3.6		0.2	V
			I_{OL} = 6 mA	2.7		0.4	V
			I_{OL} = 8 mA	3.0		0.55	V
			I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	Control Pins	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	µA
		Data Pins	$0 \leq V_I \leq V_{CC}$	2.7–3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum Drive Hold Current		V_{IN} = 0.8V	3.0	75		µA
			V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive Current to Change State		(Note 5)	3.6	450		µA
			(Note 6)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \leq (V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7–3.6		20	µA
			$V_{CC} \leq (V_O) \leq 3.6V$ (Note 7)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		$V_{IH} = V_{CC}$ −0.6V	2.7–3.6		750	µA

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
			$I_{OH} = -4$ mA	2.3	2.0		V
			$I_{OH} = -6$ mA	2.3	1.8		V
			$I_{OH} = -8$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
			$I_{OL} = 6$ mA	2.3		0.4	V
			$I_{OL} = 8$ mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3–2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		$V_{IN} = 0.7V$	2.3	45		μA
	Drive Hold Current		$V_{IN} = 1.6V$	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 8)	2.7	300		μA
	Current to Change State		(Note 9)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 10)	2.3–2.7		±20	μA

Note 8: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 9: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 10: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65-2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65-2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		$I_{OH} = -100\ \mu A$	1.65-2.3	$V_{CC} - 0.2$		V
			$I_{OH} = -3$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		$I_{OL} = 100\ \mu A$	1.65-2.3		0.2	V
			$I_{OL} = 3$mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65-2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65-2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		$V_{IN} = 0.57V$	1.65	25		μA
	Drive Hold Current		$V_{IN} = 1.07V$	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 11)	1.95	200		μA
	Current to Change State		(Note 12)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65-2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65-2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 13)	1.65-2.3		±20	μA

Note 11: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 12: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 13: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 14)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.3	1.0	3.8	1.5	7.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	5.1	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.6	1.0	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 15)		0.5		0.5		0.75	ns

Note 14: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

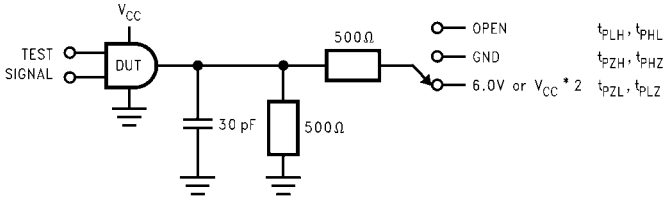
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.15	
			2.5	–0.25	V
			3.3	–0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8 ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

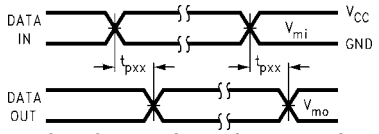


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

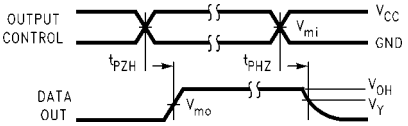


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

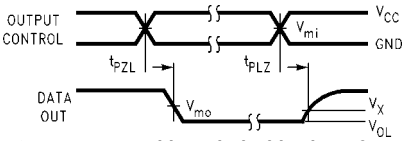
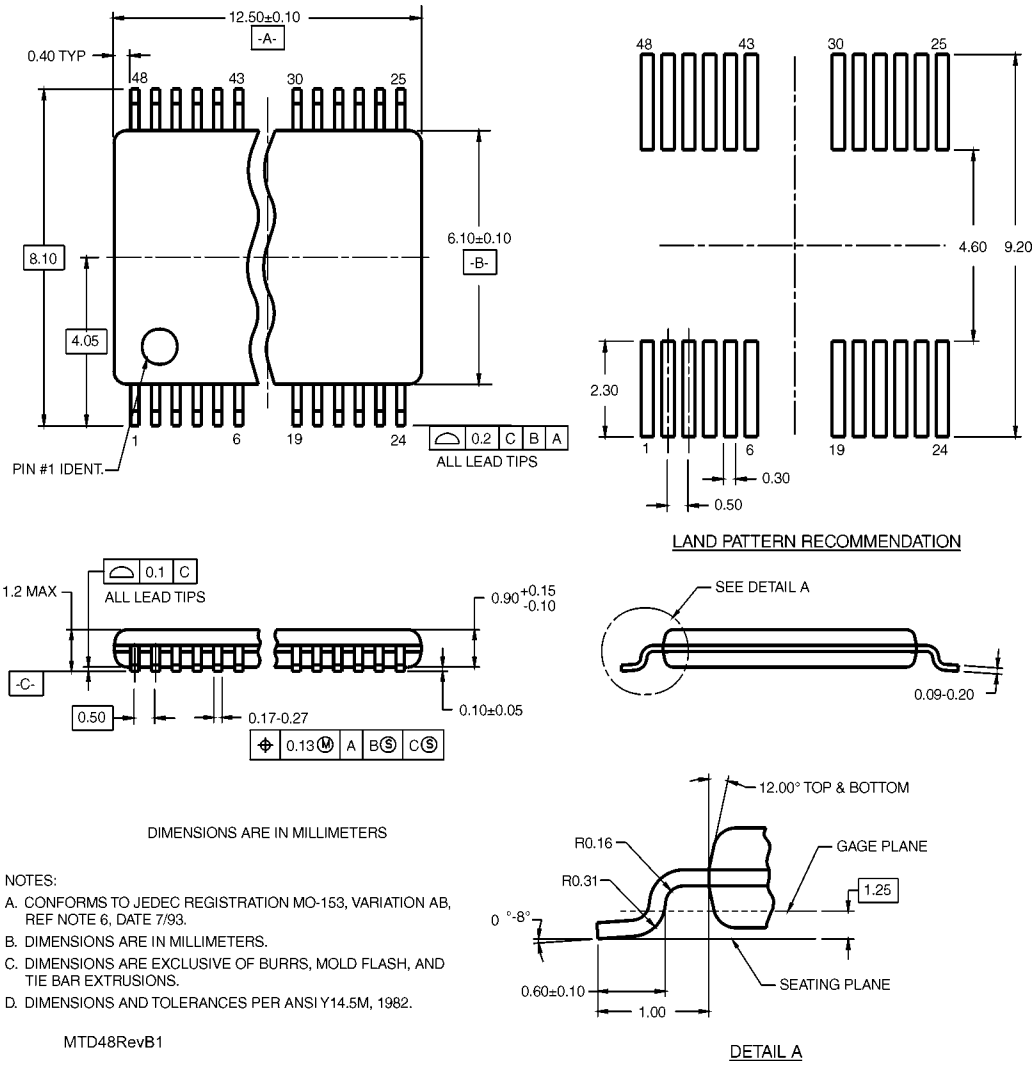


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-, 6.1mm Wide
Package Number MTD48

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January 2000
Revised January 2000

74VCXH162373
Low Voltage 16-Bit Transparent Latch with Bushold and 26Ω Series Resistors in Outputs

General Description

The VCXH162373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear to be transparent to the data when the Latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The VCXH162373 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The VCXH162373 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address driver, clock drivers and bus transceivers/transmitters.

The 74VCXH162373 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output compatibility up to 3.6V.

The 74VCXH162373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

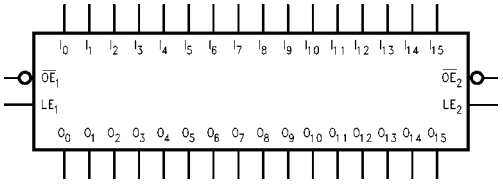
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- 26Ω series resistors in outputs
- t_{PD} (I_n to O_n)
  - 3.3 ns max for 3.0V to 3.6V V_{CC}
  - 4.5 ns max for 2.3V to 2.7V V_{CC}
  - 9.0 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Ordering Number	Package Number	Package Description
74VCXH162373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TUBES]
74VCXH162373MTX (Note 1)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

Note 1: Use this Order Number to receive devices in Tape and Reel.

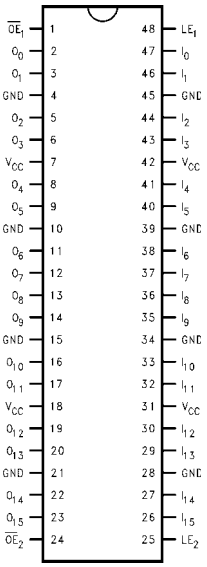
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Bushold Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

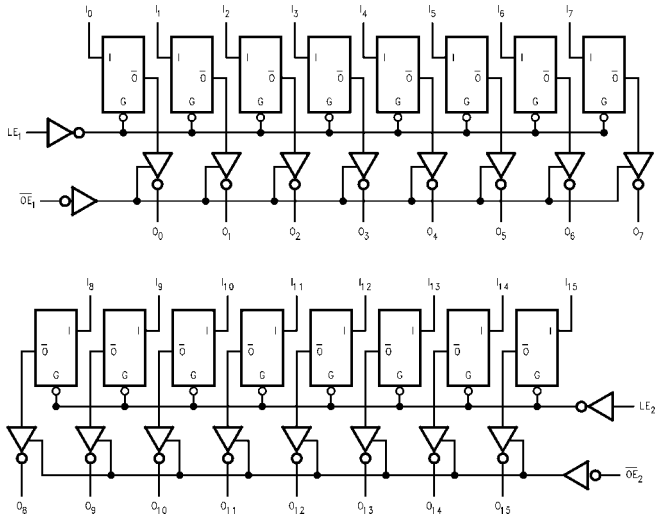
Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, control inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCXH162373 contains sixteen edge D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition on LE_n. The 3-STATE outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$, LE_n	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
			I_{OH} = −6 mA	2.7	2.2		V
			I_{OH} = −8 mA	3.0	2.4		V
			I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7–3.6		0.2	V
			I_{OL} = 6 mA	2.7		0.4	V
			I_{OL} = 8 mA	3.0		0.55	V
			I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	Control Pins	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	µA
		Data Pins	$0 \leq V_I \leq V_{CC}$	2.7–3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum Drive Hold Current		V_{IN} = 0.8V	3.0	75		µA
			V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive Current to Change State		(Note 5)	3.6	450		µA
			(Note 6)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \leq (V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7–3.6		20	µA
			$V_{CC} \leq (V_O) \leq 3.6V$ (Note 7)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		$V_{IH} = V_{CC}$ −0.6V	2.7–3.6		750	µA

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	2.3 – 2.7	V_{CC} − 0.2		V
			I_{OH} = −4 mA	2.3	2.0		V
			I_{OH} = −6 mA	2.3	1.8		V
			I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	2.3 – 2.7		0.2	V
			I_{OL} = 6 mA	2.3		0.4	V
			I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3 – 2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.7V	2.3	45		μA
	Drive Hold Current		V_{IN} = 1.6V	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 8)	2.7	300		μA
	Current to Change State		(Note 9)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 10)	2.3 – 2.7		±20	μA

Note 8: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 9: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 10: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	1.65 - 2.3	V_{CC} − 0.2		V
			I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	1.65 - 2.3		0.2	V
			I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65 - 2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.57V	1.65	25		μA
	Drive Hold Current		V_{IN} = 1.07V	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 11)	1.95	200		μA
	Current to Change State		(Note 12)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 13)	1.65 – 2.3		±20	μA

Note 11: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 12: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 13: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 14)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n	0.8	3.3	1.0	4.5	1.5	9.0	ns
t_{PHL}, t_{PLH}	Prop Delay LE to O_n	0.8	3.6	1.0	4.9	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.9	1.0	5.4	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.0	1.0	4.4	1.5	7.9	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 15)		0.5		0.5		0.75	ns

Note 14: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

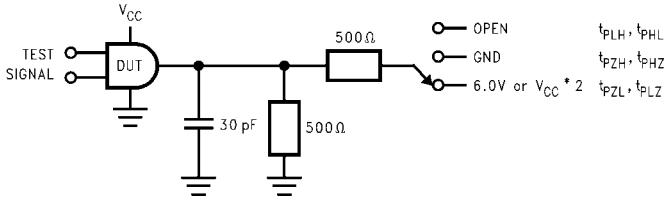
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	V
			2.5	0.25	
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.15	V
			2.5	−0.25	
			3.3	−0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	V
			2.5	2.05	
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

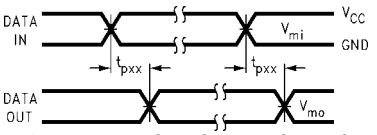


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

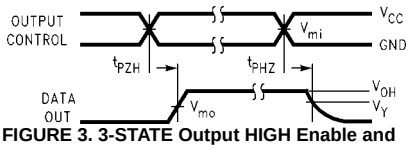


FIGURE 3. 3-STATE Output HIGH Enable and Disable Times for Low Voltage Logic

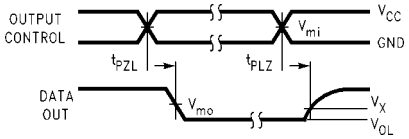


FIGURE 4. 3-STATE Output LOW Enable and Disable Times for Low Voltage Logic

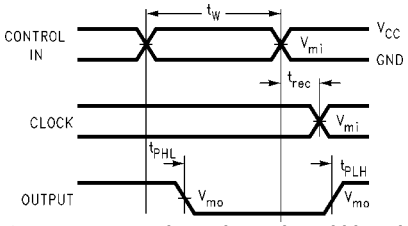


FIGURE 5. Propagation Delay, Pulse Width and t_{REC} Waveforms

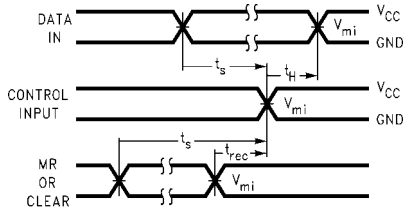
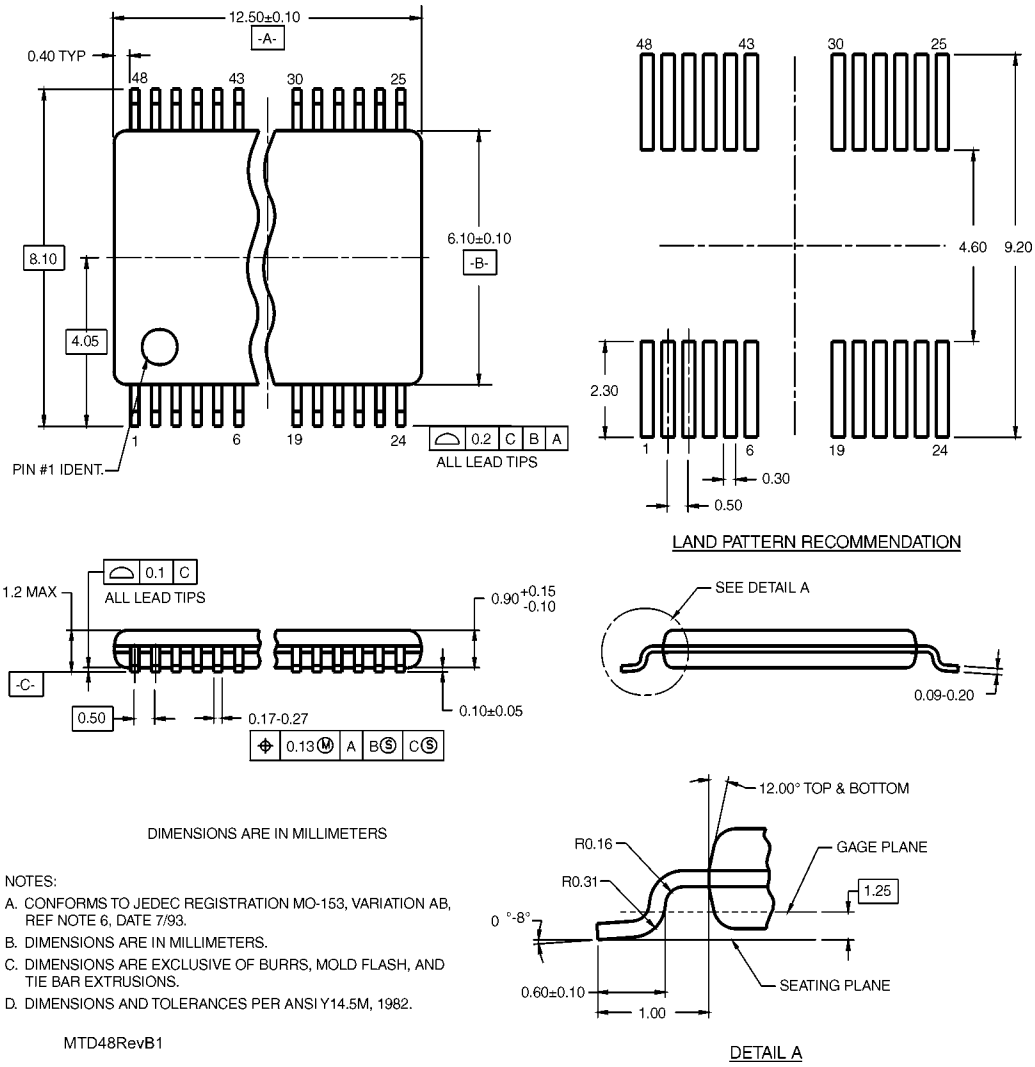


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74VCXH162374
Low Voltage 16-Bit D-Type Flip-Flop with Bushold and 26Ω Series Resistors in Outputs

General Description

The VCXH162374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and output enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

The VCXH162374 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH162374 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers and bus transceivers/transmitters.

The 74VCXH162374 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output compatibility up to 3.6V.

The 74VCXH162374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

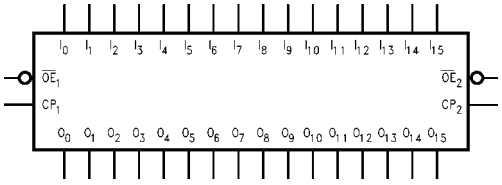
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold data inputs eliminates the need for external pull-up/pull-down resistors
- 26Ω series resistors in outputs
- t_{PD} (CLK to O_n)
  - 3.4 ns max for 3.0V to 3.6V V_{CC}
  - 4.8 ns max for 2.3V to 2.7V V_{CC}
  - 9.6 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCXH162374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TUBES]
74VCXH162374MTX (Note 1)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

Note 1: Use this Order Number to receive devices in Tape and Reel.

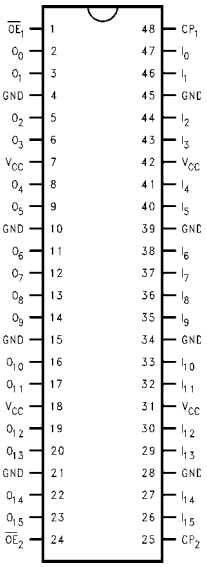
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Bushold Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
↑	L	H	H
↑	L	L	L
L	L	X	O_0
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
↑	L	H	H
↑	L	L	L
L	L	X	O_0
X	H	X	Z

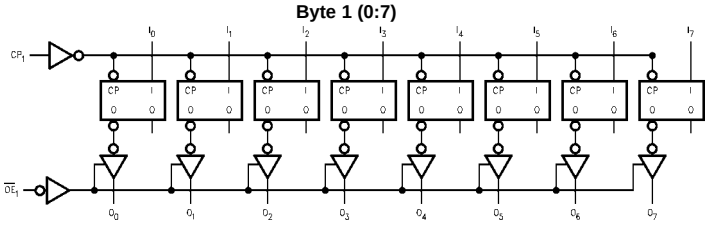
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, control inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of CP

Functional Description

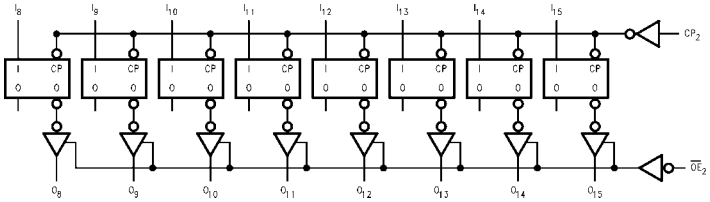
The 74VCXH162374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each clock has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual I inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operations of the $\overline{OE}_n$ input does not affect the state of the flip-flops.

Logic Diagram

Byte 1 (0:7)



Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$, CP_n	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} to 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 3)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
$V_I < 0V$	−50 mA
DC Output Diode Current (I_{OK})	
$V_O < 0V$	−50 mA
$V_O > V_{CC}$	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 4)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} = 1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
			I_{OH} = −6 mA	2.7	2.2		V
			I_{OH} = −8 mA	3.0	2.4		V
			I_{OH} = −12 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7 – 3.6		0.2	V
			I_{OL} = 6 mA	2.7		0.4	V
			I_{OL} = 8 mA	3.0		0.55	V
			I_{OL} = 12 mA	3.0		0.8	V
I_I	Input Leakage Current	Control Pins	$0 \leq V_I \leq 3.6V$	2.7 – 3.6		±5.0	µA
		Data Pins	$0 \leq V_I \leq V_{CC}$	2.7 – 3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current		V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 5)	3.6	450		µA
	Current to Change State		(Note 6)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \leq (V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7 – 3.6		20	µA
			$V_{CC} \leq (V_O) \leq 3.6V$ (Note 7)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		$V_{IH} = V_{CC}$ −0.6V	2.7 – 3.6		750	µA

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	2.3 – 2.7	V_{CC} − 0.2		V
			I_{OH} = −4 mA	2.3	2.0		V
			I_{OH} = −6 mA	2.3	1.8		V
			I_{OH} = −8 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	2.3 – 2.7		0.2	V
			I_{OL} = 6 mA	2.3		0.4	V
			I_{OL} = 8 mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3 – 2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.7V	2.3	45		μA
	Drive Hold Current		V_{IN} = 1.6V	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 8)	2.7	300		μA
	Current to Change State		(Note 9)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 10)	2.3 – 2.7		±20	μA

Note 8: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 9: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 10: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	1.65 - 2.3	V_{CC} − 0.2		V
			I_{OH} = −3 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	1.65 - 2.3		0.2	V
			I_{OL} = 3 mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65 - 2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.57V	1.65	25		μA
	Drive Hold Current		V_{IN} = 1.07V	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 11)	1.95	200		μA
	Current to Change State		(Note 12)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 13)	1.65 - 2.3		±20	μA

Note 11: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 12: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 13: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 14)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay CP to O_n	0.8	3.4	1.0	4.8	1.5	9.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.9	1.0	5.4	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	4.0	1.0	4.4	1.5	7.9	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 15)		0.5		0.5		0.75	ns

Note 14: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

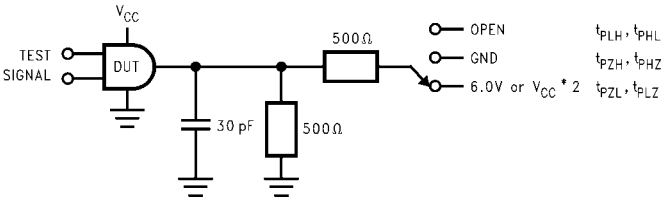
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.15	
			2.5	−0.25	V
			3.3	−0.35	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

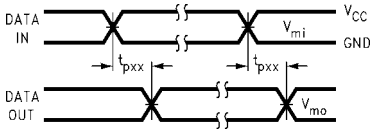


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

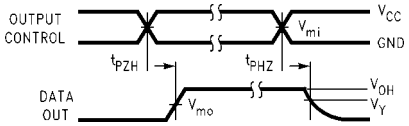


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

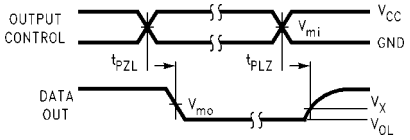


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

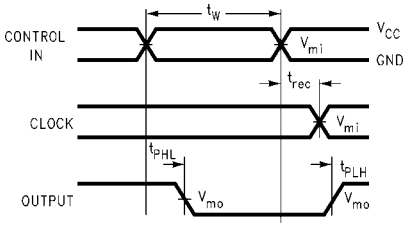


FIGURE 5. Propagation Delay, Pulse Width and t_{REC} Waveforms

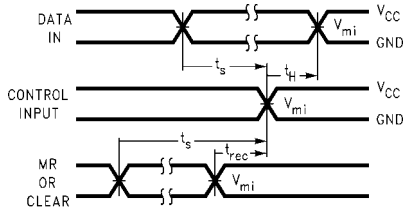
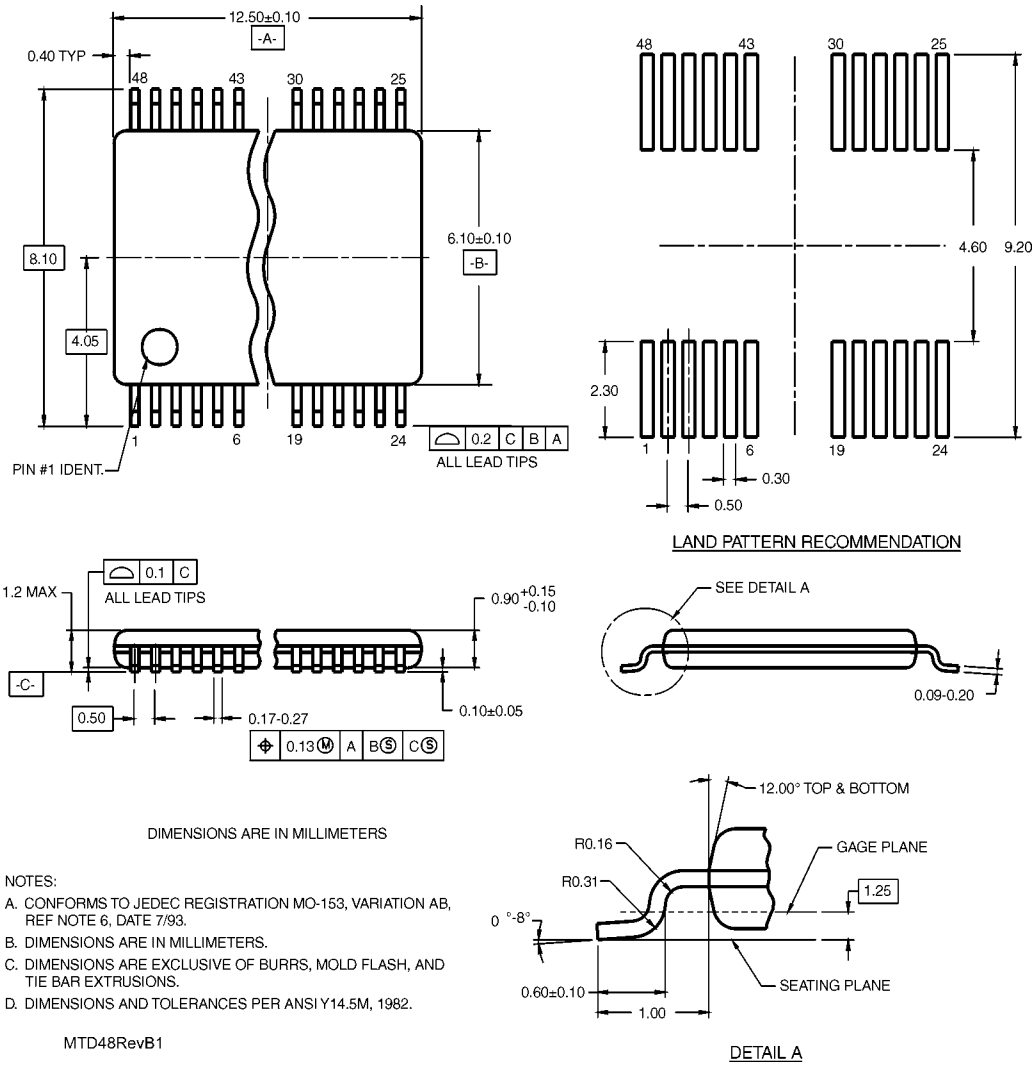


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Body Width
Package Number MTD48

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FAIRCHILD SEMICONDUCTOR™

December 1999
Revised December 1999

74VCXH16240
Low Voltage 16-Bit Inverting Buffer/Line Driver with Bushold

General Description

The VCXH16240 contains sixteen inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The VCXH16240 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating inputs at a valid logic level.

The 74VCXH16240 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output capability up to 3.6V.

The 74VCXH16240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

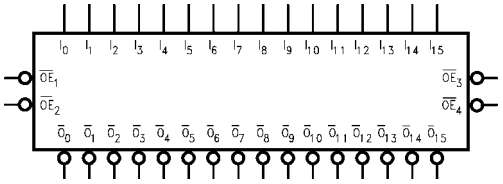
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- t_{PD}
  - 2.5 ns max for 3.0V to 3.6V V_{CC}
  - 3.0 ns max for 2.3V to 2.7V V_{CC}
  - 6.0 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCXH16240MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

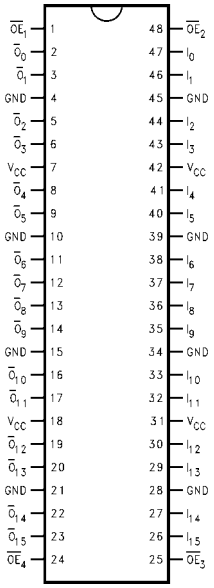
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Bushold Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

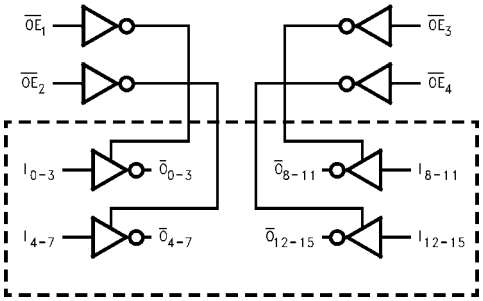
Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCXH16240 contains sixteen inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 2)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
			I_{OH} = −12 mA	2.7	2.2		V
			I_{OH} = −18 mA	3.0	2.4		V
			I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7 – 3.6		0.2	V
			I_{OL} = 12 mA	2.7		0.4	V
			I_{OL} = 18 mA	3.0		0.4	V
			I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	Control Pins	$0 \leq V_I \leq 3.6V$	2.7 – 3.6		±5.0	µA
		Data Pins	$0 \leq V_I \leq V_{CC}$	2.7 – 3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current		V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 4)	3.6	450		µA
	Current to Change State		(Note 5)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \leq (V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7 – 3.6		20	µA
			$V_{CC} \leq (V_O) \leq 3.6V$ (Note 6)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		$V_{IH} = V_{CC}$ −0.6V	2.7 – 3.6		750	µA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must source at least the specified current to switch from HIGH-to-LOW.

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = –100 µA	2.3 – 2.7	V_{CC} – 0.2		V
			I_{OH} = –6 mA	2.3	2.0		V
			I_{OH} = –12 mA	2.3	1.8		V
			I_{OH} = –18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.3 – 2.7		0.2	V
			I_{OL} = 12 mA	2.3		0.4	V
			I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	µA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3 – 2.7		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.7V	2.3	45		µA
	Drive Hold Current		V_{IN} = 1.6V	2.3	–45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 7)	2.7	300		µA
	Current to Change State		(Note 8)	2.7	–300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	µA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 9)	2.3 – 2.7		±20	µA

Note 7: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 8: An external driver must source at least the specified current to switch from HIGH-to-LOW.

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = –100 µA	1.65 - 2.3	V_{CC} – 0.2		V
			I_{OH} = –6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	1.65 - 2.3		0.2	V
			I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	µA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65 - 2.3		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.57V	1.65	25		µA
	Drive Hold Current		V_{IN} = 1.07V	1.65	–25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 10)	1.95	200		µA
	Current to Change State		(Note 11)	1.95	–200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	µA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 12)	1.65 – 2.3		±20	µA

Note 10: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 11: An external driver must source at least the specified current to switch from HIGH-to-LOW.

Note 12: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 13)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.1	1.5	8.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 14)		0.5		0.5		0.75	ns

Note 13: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

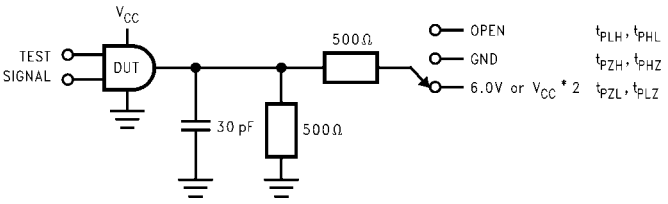
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC}	$T_A = +25°C$	Units
			(V)	Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	
			2.5	–0.6	V
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

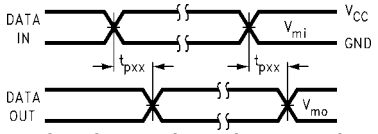


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

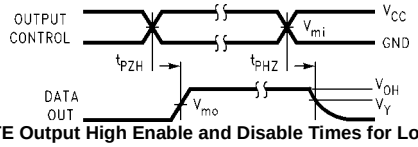


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

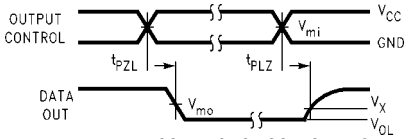
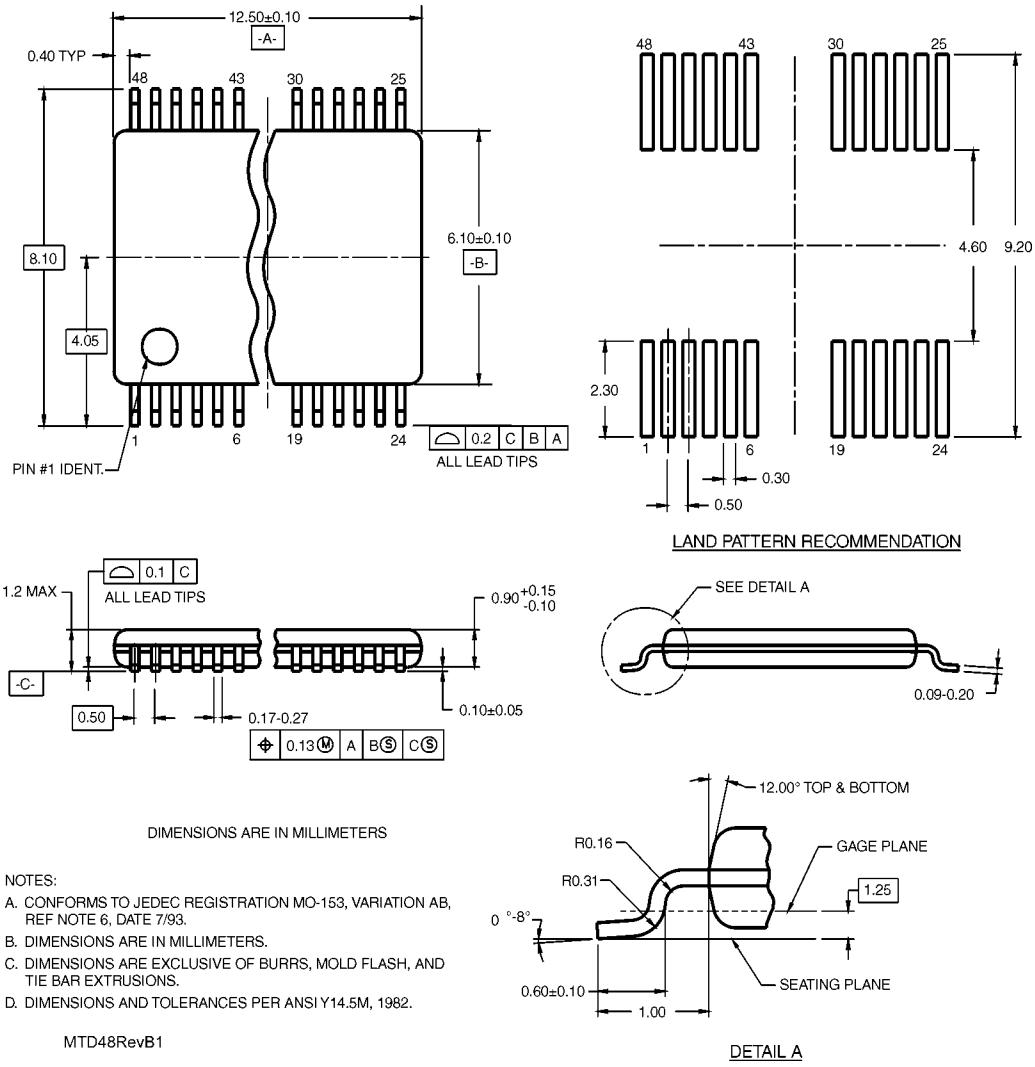


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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FAIRCHILD SEMICONDUCTOR™

November 1999
Revised December 1999

74VCXH16244
Low Voltage 16-Bit Buffer/Line Driver with Bushold

General Description

The VCXH16244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The VCXH16244 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH16244 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output capability up to 3.6V.

The 74VCXH16244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

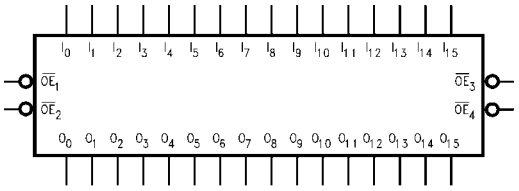
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- t_{PD}
  - 2.5 ns max for 3.0V to 3.6V V_{CC}
  - 3.0 ns max for 2.3V to 2.7V V_{CC}
  - 6.0 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description
74VCXH16244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

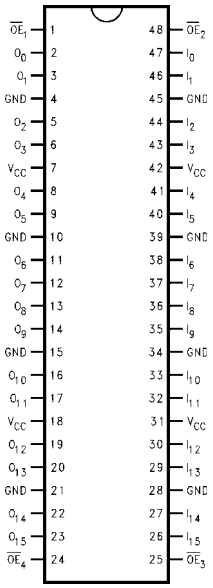
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
I_0–I_{15}	Bushold Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	O_0–O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8-I_{11}	O_8–O_{11}
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4-I_7	O_4-O_7
L	L	L
L	H	H
H	X	Z

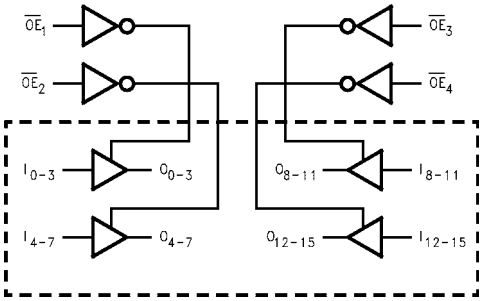
Inputs		Outputs
$\overline{OE}_4$	I_{12}-I_{15}	O_{12}-O_{15}
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCXH16244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation.The 3-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW, the outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 2)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
			I_{OH} = −12 mA	2.7	2.2		V
			I_{OH} = −18 mA	3.0	2.4		V
			I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7–3.6		0.2	V
			I_{OL} = 12 mA	2.7		0.4	V
			I_{OL} = 18 mA	3.0		0.4	V
			I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	Control Pins	$0 \leq V_I \leq 3.6V$	2.7–3.6		±5.0	µA
		Data Pins	$0 \leq V_I \leq V_{CC}$	2.7–3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current		V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 4)	3.6	450		µA
	Current to Change State		(Note 5)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		$0 \leq (V_O) \leq 3.6V$	0		10	µA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7–3.6		20	µA
			$V_{CC} \leq (V_O) \leq 3.6V$ (Note 6)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		$V_{IH} = V_{CC}$ −0.6V	2.7–3.6		750	µA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
			$I_{OH} = -6$ mA	2.3	2.0		V
			$I_{OH} = -12$ mA	2.3	1.8		V
			$I_{OH} = -18$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
			$I_{OL} = 12$ mA	2.3		0.4	V
			$I_{OL} = 18$ mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3–2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		$V_{IN} = 0.7V$	2.3	45		μA
	Drive Hold Current		$V_{IN} = 1.6V$	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 7)	2.7	300		μA
	Current to Change State		(Note 8)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3–2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 9)	2.3–2.7		±20	μA

Note 7: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 8: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65–2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65–2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		$I_{OH} = -100\ \mu A$	1.65–2.3	$V_{CC} - 0.2$		V
			$I_{OH} = -6$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		$I_{OL} = 100\ \mu A$	1.65–2.3		0.2	V
			$I_{OL} = 6$ mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65–2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		$V_{IN} = 0.57V$	1.65	25		μA
	Drive Hold Current		$V_{IN} = 1.07V$	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 10)	1.95	200		μA
	Current to Change State		(Note 11)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65–2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65–2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 12)	1.65–2.3		±20	μA

Note 10: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 11: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 12: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 13)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	2.5	1.0	3.0	1.5	6.0	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.1	1.5	8.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 14)		0.5		0.5		0.75	ns

Note 13: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

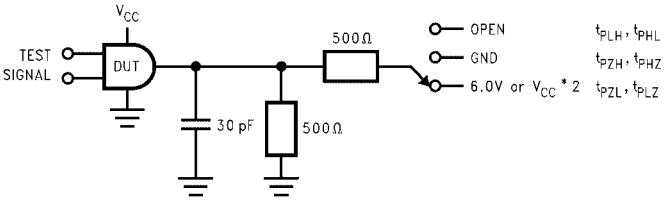
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

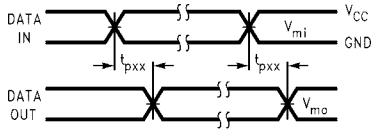


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

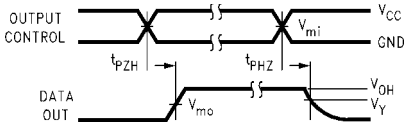


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

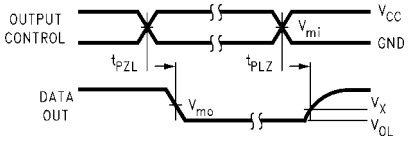
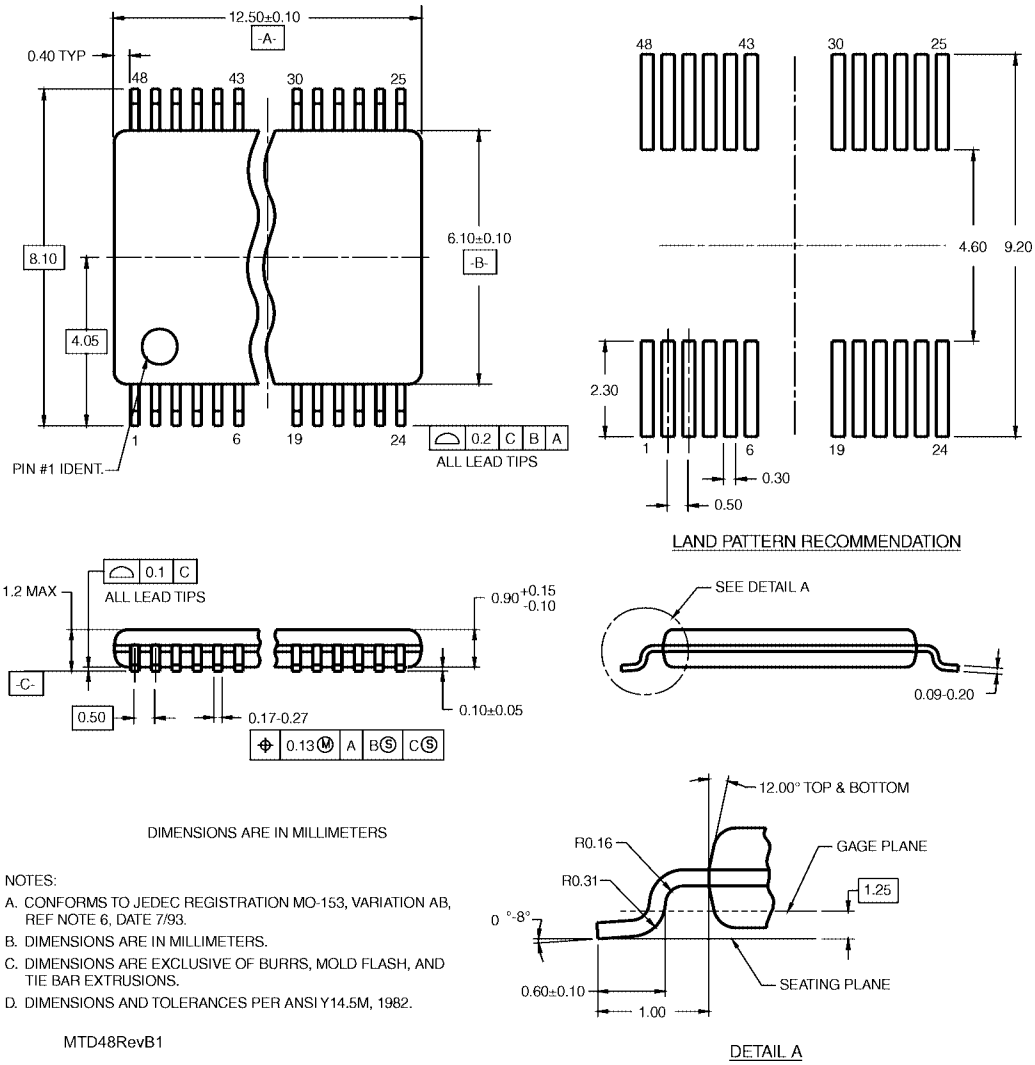


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74VCXH16373
Low Voltage 16-Bit Transparent Latch with Bushold

General Description

The VCXH16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear to be transparent to the data when the Latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{OE}$) is LOW. When $\overline{OE}$ is HIGH, the outputs are in a high impedance state.

The VCXH16373 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH16373 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output compatibility up to 3.6V.

The 74VCXH16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

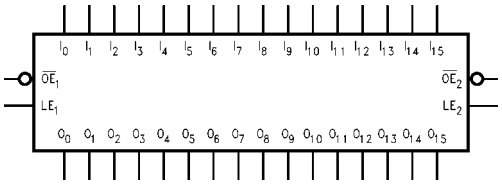
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- t_{PD} (I_n to O_n)
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 3.4 ns max for 2.3V to 2.7V V_{CC}
  - 6.8 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Ordering Number	Package Number	Package Description
74VCXH16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

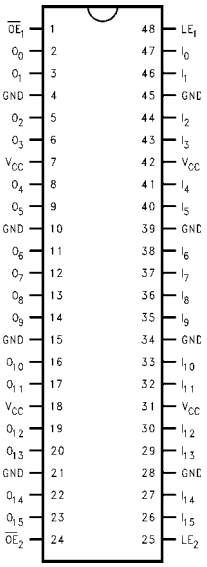
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
LE_n	Latch Enable Input
I_0–I_{15}	Bushold Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
LE_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

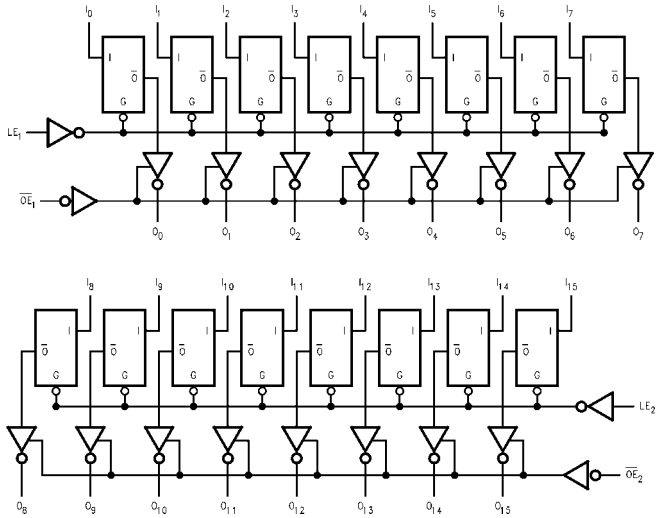
Inputs			Outputs
LE_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, control inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCXH16373 contains sixteen edge D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition on LE_n. The 3-STATE outputs are controlled by the Output Enable ($\overline{OE}_n$) input. When $\overline{OE}_n$ is LOW the standard outputs are in the 2-state mode. When $\overline{OE}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$, LE_n	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 2)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
			I_{OH} = −12 mA	2.7	2.2		V
			I_{OH} = −18 mA	3.0	2.4		V
			I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7–3.6		0.2	V
			I_{OL} = 12 mA	2.7		0.4	V
			I_{OL} = 18 mA	3.0		0.4	V
			I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	Control Pins	0 ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
		Data Pins	0 ≤ V_I ≤ V_{CC}	2.7–3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current		V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 4)	3.6	450		µA
	Current to Change State		(Note 5)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		0 ≤ (V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current		V_I = V_{CC} or GND	2.7–3.6		20	µA
			V_{CC} ≤ (V_O) ≤ 3.6V (Note 6)	2.7–3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		$I_{OH} = -100\ \mu A$	2.3 – 2.7	$V_{CC} - 0.2$		V
			$I_{OH} = -6$ mA	2.3	2.0		V
			$I_{OH} = -12$ mA	2.3	1.8		V
			$I_{OH} = -18$ mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		$I_{OL} = 100\ \mu A$	2.3 – 2.7		0.2	V
			$I_{OL} = 12$ mA	2.3		0.4	V
			$I_{OL} = 18$ mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3 – 2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		$V_{IN} = 0.7V$	2.3	45		μA
	Drive Hold Current		$V_{IN} = 1.6V$	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 7)	2.7	300		μA
	Current to Change State		(Note 8)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$	2.3 – 2.7		±10	μA
			$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 9)	2.3 – 2.7		±20	μA

Note 7: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 8: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
			$I_{OH} = -6$ mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
			$I_{OL} = 6$ mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65 – 2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65 – 2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		$V_{IN} = 0.57V$	1.65	25		μA
	Drive Hold Current		$V_{IN} = 1.07V$	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 10)	1.95	200		μA
	Current to Change State		(Note 11)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	μA
			$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 12)	1.65 – 2.3		±20	μA

Note 10: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 11: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 12: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 13)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay I_n to O_n	0.8	3.0	1.0	3.4	1.5	6.8	ns
t_{PHL}, t_{PLH}	Prop Delay LE to O_n	0.8	3.0	1.0	3.9	1.5	7.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.6	1.5	9.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 14)		0.5		0.5		0.75	ns

Note 13: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

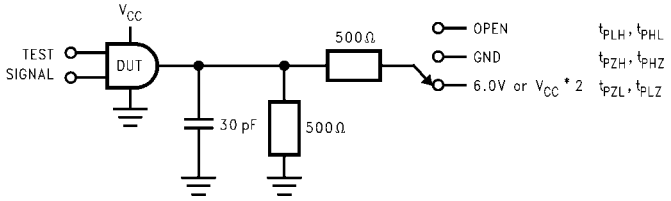
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

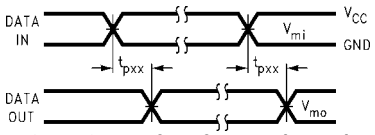


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

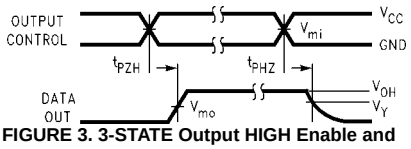


FIGURE 3. 3-STATE Output HIGH Enable and Disable Times for Low Voltage Logic

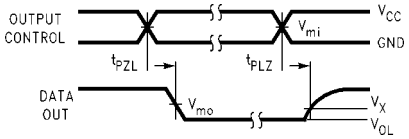


FIGURE 4. 3-STATE Output LOW Enable and Disable Times for Low Voltage Logic

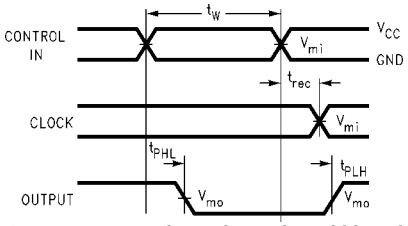


FIGURE 5. Propagation Delay, Pulse Width and t_{REC} Waveforms

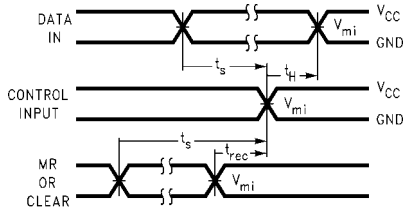
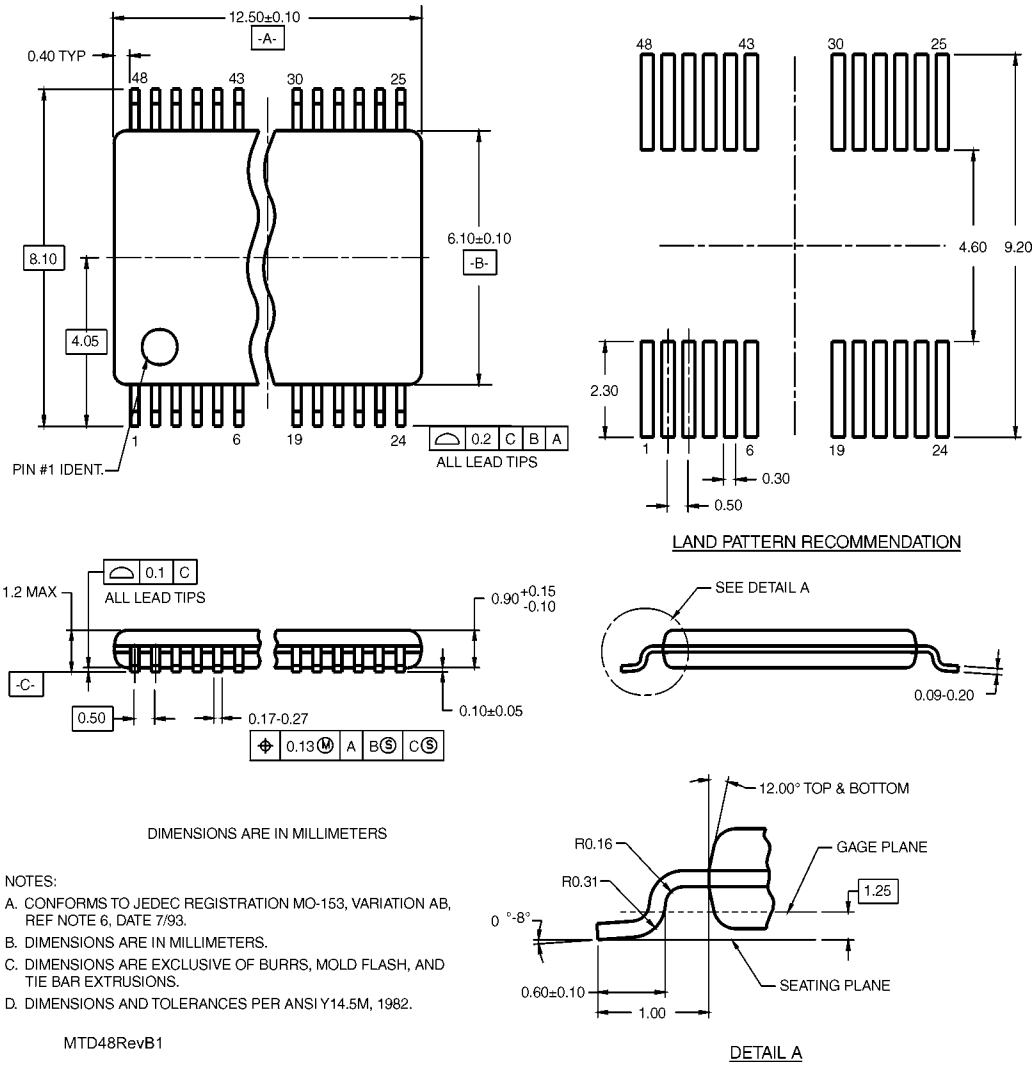


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 2000
Revised January 2000

74VCXH16374
Low Voltage 16-Bit D-Type Flip-Flop with Bushold

General Description

The VCXH16374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and output enable ($\overline{OE}$) are common to each byte and can be shorted together for full 16-bit operation.

The VCXH16374 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH16374 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output compatibility up to 3.6V.

The 74VCXH16374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

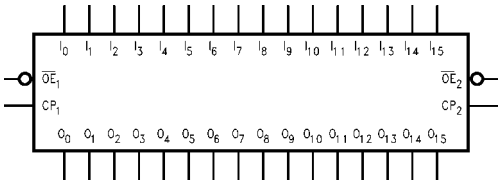
- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- t_{PD}
  - 3.0 ns max for 3.0V to 3.6V V_{CC}
  - 3.9 ns max for 2.3V to 2.7V V_{CC}
  - 7.8 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Descriptions
74VCXH16374MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

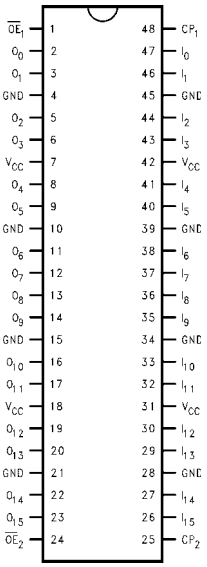
Logic Symbol



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Input (Active LOW)
CP_n	Clock Pulse Input
I_0–I_{15}	Bushold Inputs
O_0–O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs			Outputs
CP_1	$\overline{OE}_1$	I_0–I_7	O_0–O_7
⌐	L	H	H
⌐	L	L	L
L	L	X	O_0
X	H	X	Z

Inputs			Outputs
CP_2	$\overline{OE}_2$	I_8–I_{15}	O_8–O_{15}
⌐	L	H	H
⌐	L	L	L
L	L	X	O_0
X	H	X	Z

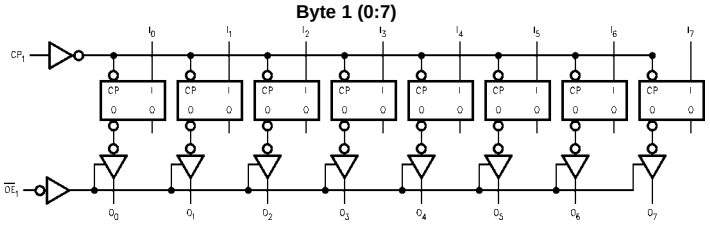
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, control inputs may not float)
Z = High Impedance
O_0 = Previous O_0 before HIGH-to-LOW of CP

Functional Description

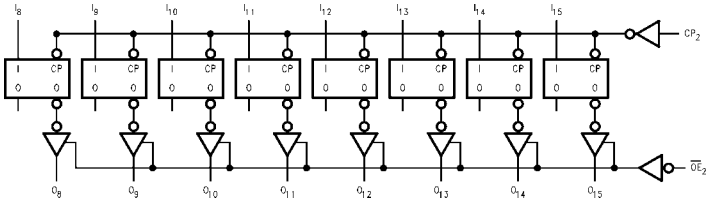
The 74VCXH16374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each clock has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual I inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable ($\overline{OE}_n$) LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}_n$ is HIGH, the outputs go to the high impedance state. Operations of the $\overline{OE}_n$ input does not affect the state of the flip-flops.

Logic Diagram

Byte 1 (0:7)



Byte 2 (8:15)



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$\overline{OE}_n$, CP_n	−0.5V to 4.6V
$I_0 - I_{15}$	−0.5V to V_{CC} + 0.5V
Output Voltage (V_O)	
Outputs 3-STATED	−0.5V to +4.6V
Outputs Active (Note 2)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in "OFF" State	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.7 – 3.6	2.0		V
V_{IL}	LOW Level Input Voltage			2.7 – 3.6		0.8	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 µA	2.7 – 3.6	V_{CC} − 0.2		V
			I_{OH} = −12 mA	2.7	2.2		V
			I_{OH} = −18 mA	3.0	2.4		V
			I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 µA	2.7 – 3.6		0.2	V
			I_{OL} = 12 mA	2.7		0.4	V
			I_{OL} = 18 mA	3.0		0.4	V
			I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	Control Pins	0 ≤ V_I ≤ 3.6V	2.7 – 3.6		±5.0	µA
		Data Pins	0 ≤ V_I ≤ V_{CC}	2.7 – 3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current		V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 4)	3.6	450		µA
	Current to Change State		(Note 5)	3.6	−450		
I_{OZ}	3-STATE Output Leakage		0 ≤ V_O ≤ 3.6V V_I = V_{IH} or V_{IL}	2.7 – 3.6		±10	µA
I_{OFF}	Power-OFF Leakage Current		0 ≤ (V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current		V_I = V_{CC} or GND	2.7 – 3.6		20	µA
			V_{CC} ≤ (V_O) ≤ 3.6V (Note 6)	2.7 – 3.6		±20	µA
ΔI_{CC}	Increase in I_{CC} per Input		V_{IH} = V_{CC} −0.6V	2.7 – 3.6		750	µA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V_{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	2.3 – 2.7	V_{CC} − 0.2		V
			I_{OH} = −6 mA	2.3	2.0		V
			I_{OH} = −12 mA	2.3	1.8		V
			I_{OH} = −18 mA	2.3	1.7		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	2.3 – 2.7		0.2	V
			I_{OL} = 12 mA	2.3		0.4	V
			I_{OL} = 18 mA	2.3		0.6	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	2.3 – 2.7		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	2.3 – 2.7		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.7V	2.3	45		μA
	Drive Hold Current		V_{IN} = 1.6V	2.3	-45		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 7)	2.7	300		μA
	Current to Change State		(Note 8)	2.7	−300		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 – 2.7		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 9)	2.3 – 2.7		±20	μA

Note 7: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 8: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter		Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage		I_{OH} = −100 μA	1.65 - 2.3	V_{CC} − 0.2		V
			I_{OH} = −6 mA	1.65	1.25		V
V_{OL}	LOW Level Output Voltage		I_{OL} = 100 μA	1.65 - 2.3		0.2	V
			I_{OL} = 6 mA	1.65		0.3	V
I_I	Input Leakage Current	Control Pins	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
		Data Pins	$0 \le V_I \le V_{CC}$	1.65 - 2.3		±5.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum		V_{IN} = 0.57V	1.65	25		μA
	Drive Hold Current		V_{IN} = 1.07V	1.65	-25		
$I_{I(OD)}$	Bushold Input Over-Drive		(Note 10)	1.95	200		μA
	Current to Change State		(Note 11)	1.95	−200		
I_{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μA
I_{OFF}	Power-OFF Leakage Current		$0 \le (V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
			$V_{CC} \le (V_O) \le 3.6V$ (Note 12)	1.65 - 2.3		±20	μA

Note 10: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 11: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 12: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 13)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		100		MHz
t_{PHL}, t_{PLH}	Prop Delay CP to O_n	0.8	3.0	1.0	3.9	1.5	7.8	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.5	1.0	4.6	1.5	9.2	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 14)		0.5		0.5		0.75	ns

Note 13: For $C_L = 50_P$F, add approximately 300 ps to the AC maximum specification.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

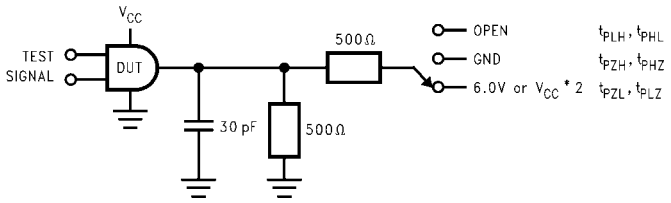
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.25	V
			2.5	0.6	
			3.3	0.8	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	–0.25	V
			2.5	–0.6	
			3.3	–0.8	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.5	V
			2.5	1.9	
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
C_{OUT}	Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

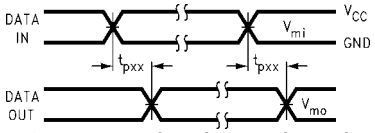


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

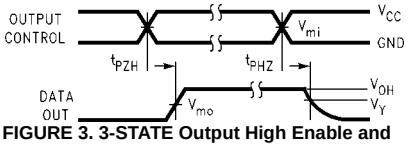


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

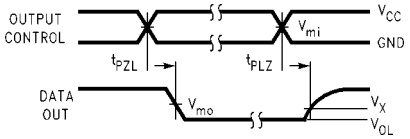


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

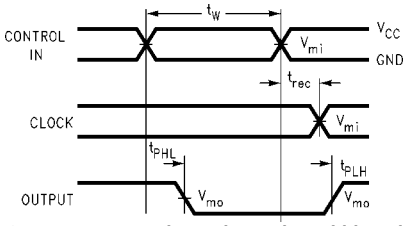


FIGURE 5. Propagation Delay, Pulse Width and t_{REC} Waveforms

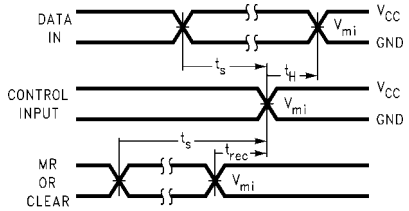
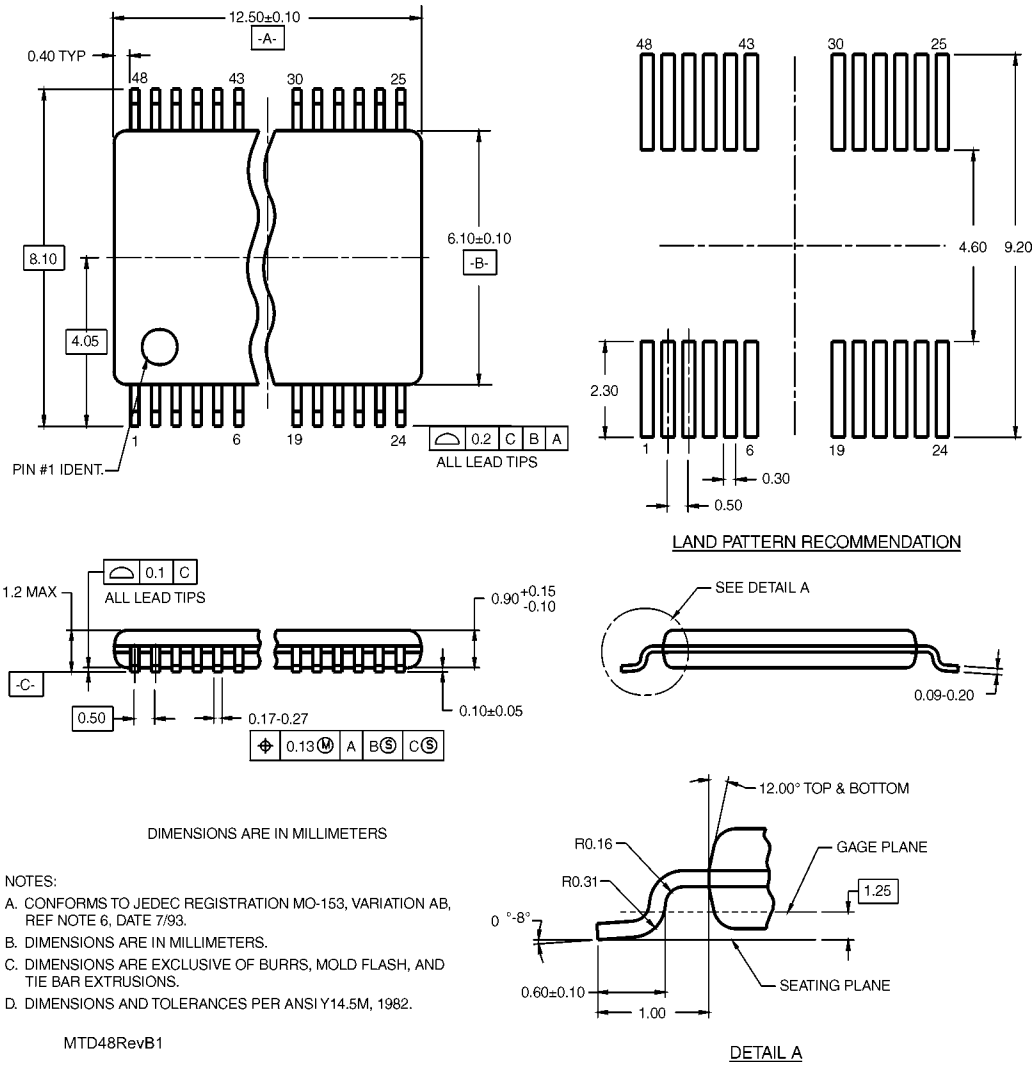


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} −0.3V	V_{OH} −0.15V	V_{OH} −0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



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B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48RevB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Body Width
Package Number MTD48

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1999
Revised July 1999

74VCXH2245
Low Voltage Bidirectional Transceiver with Bushold and 26Ω Series Resistors in B Outputs

General Description

The VCXH2245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The T/$\overline{R}$ input determines the direction of data flow. The $\overline{OE}$ input disables both the A and B Ports by placing them in a high impedance state. The VCXH2245 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH2245 is designed for low voltage (1.65V to 3.6V) V_{CC} applications. The VCXH2245 is also designed with 26Ω series resistance in the B Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers transmitters

The 74VCXH2245 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

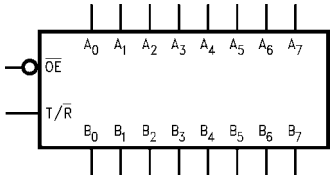
- 1.65V-3.6V V_{CC} supply operation
- 3.6V tolerant control inputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- 26Ω series resistors in B Port outputs
- t_{PD} (A to B)
  - 4.4 ns max for 3.0V to 3.6V V_{CC}
  - 5.6 ns max for 2.3V to 2.7V V_{CC}
  - 9.8 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL} B outputs):
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

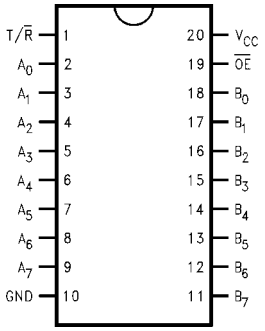
Order Number	Package Number	Package Description
74VCXH2245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VCXH2245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Pin Descriptions

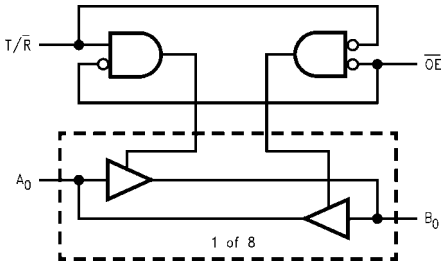
Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Bushold Inputs or 3-STATE Outputs
B_0–B_7	Side B Bushold Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
T/$\overline{R}$, $\overline{OE}$	−0.5V to 4.6 V
I/O Ports	−0.5V to V_{CC} + 0.5V
DC Output Voltage (V_O)(Note 2)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current	±100 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply Voltage (V_{CC})	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Output Current in I_{OH}/I_{OL} - A Outputs	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Output Current in I_{OH}/I_{OL} - B Outputs	
V_{CC} = 3.0V to 3.6V	± 12 mA
V_{CC} = 2.3V to 2.7V	± 8 mA
V_{CC} = 1.65V to 2.3V	± 3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics ($2.7V < V_{CC} \leq 3.6V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
	A Outputs	I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC}−0.2		V
	B Outputs	I_{OH} = −6 mA	2.7	2.2		
		I_{OH} = −8 mA	3.0	2.4		
		I_{OH} = −12 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
	A Outputs	I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
	B Outputs	I_{OL} = 6 mA	2.7		0.4	
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12 mA	3.0		0.8	
I_I	Input Leakage Current	V_{IN} = V_{CC} or GND	2.7–3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum	V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current	V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive	(Note 4)	3.6	450		µA
	Current to Change State	(Note 5)	3.6	−450		
I_{OZ}	3-STATE Output Leakage	V_O = V_{CC} or GND V_I = V_{IH} or V_{IL}	2.7–3.6		±10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC} − 0.2		V
	A Outputs	I_{OH} = −6 mA	2.3	2.0		
		I_{OH} = −12 mA	2.3	1.8		
		I_{OH} = −18 mA	2.3	1.7		
	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC}−2		V
	B Outputs	I_{OH} = −4 mA	2.3	2.0		
		I_{OH} = −6 mA	2.3	1.8		
		I_{OH} = −8mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
	A Outputs	I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
	B Outputs	I_{OL} = 6 mA	2.3		0.4	
		I_{OL} = 8 mA	2.3		0.6	
I_I	Input Leakage Current	V_{IN} = V_{CC} or GND	2.3–2.7		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum	V_{IN} = 0.7V	2.3	45		µA
	Drive Hold Current	V_{IN} = 1.6V	2.3	−45		
$I_{I(OD)}$	Bushold Input Over−Drive	(Note 6)	2.7	300		µA
	Current to Change State	(Note 7)	2.7	−300		
I_{OZ}	3-STATE Output Leakage	V_O = V_{CC} or GND	2.3–2.7		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.3–2.7		20	µA

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–1.95	V_{CC} − 0.2		V
	A Outputs	I_{OH} = −6 mA	1.65	1.25		
	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–2.3	V_{CC}−0.2		V
	B Outputs	I_{OH} = −3 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
	A Outputs	I_{OL} = 6 mA	1.65		0.3	
	LOW Level Output Voltage	I_{OL} = 100µA	1.65–2.3		0.2	V
	B Outputs	I_{OL} = 3 mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum	V_{IN} = 0.57V	1.65	25		µA
	Drive Hold Current	V_{IN} = 1.07V	1.65	−25		
$I_{I(OD)}$	Bushold Input Over-Drive	(Note 8)	1.95	200		µA
	Current to Change State	(Note 9)	1.95	−200		
I_{OZ}	3-STATE Output Leakage	V_O = V_{CC} or GND	1.65–2.3		±10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	1.65–2.3		20	µA

Note 8: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 9: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay, A to B	0.6	4.4	0.8	5.6	1.5	9.8	ns
t_{PHL} t_{PLH}	Propagation Delay, B to A	0.6	3.5	0.8	4.2	1.5	8.4	ns
t_{PZL} t_{PZH}	Output Enable Time, A to B	0.6	5.0	0.8	6.6	1.5	9.8	ns
t_{PZL} t_{PZH}	Output Enable Time, B to A	0.6	4.5	0.8	5.6	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time, A to B	0.6	4.2	0.8	4.7	1.5	8.5	ns
t_{PLZ} t_{PHZ}	Output Disable Time, B to A	0.6	3.6	0.8	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 11)		0.5		0.5		0.75	ns

Note 10: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$ Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.3 0.7 1.0	V
	Quiet Output Dynamic Peak V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.2 0.45 0.65	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	–0.3 –0.7 –1.0	V
	Quiet Output Dynamic Valley, V_{OL}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	–0.2 –0.45 –0.65	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}, B to A	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.3 1.7 2.0	V
	Quiet Output Dynamic Valley V_{OH}, A to B	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.5 2.0 2.5	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$ Typical	Units
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	6	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

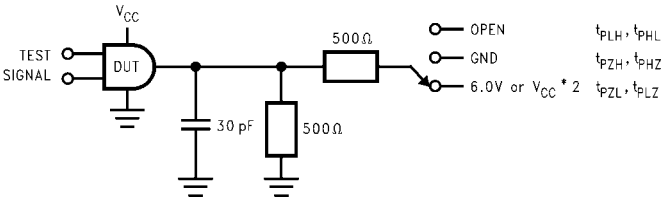


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5V ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

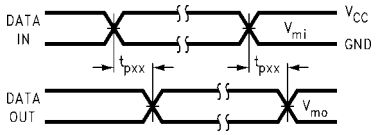


FIGURE 2. Waveform for Inverting and Non-inverting Functions

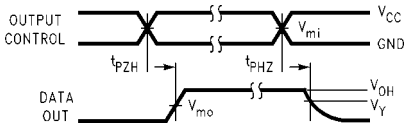


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

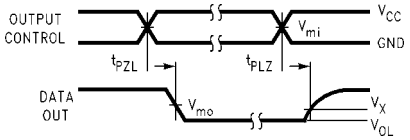
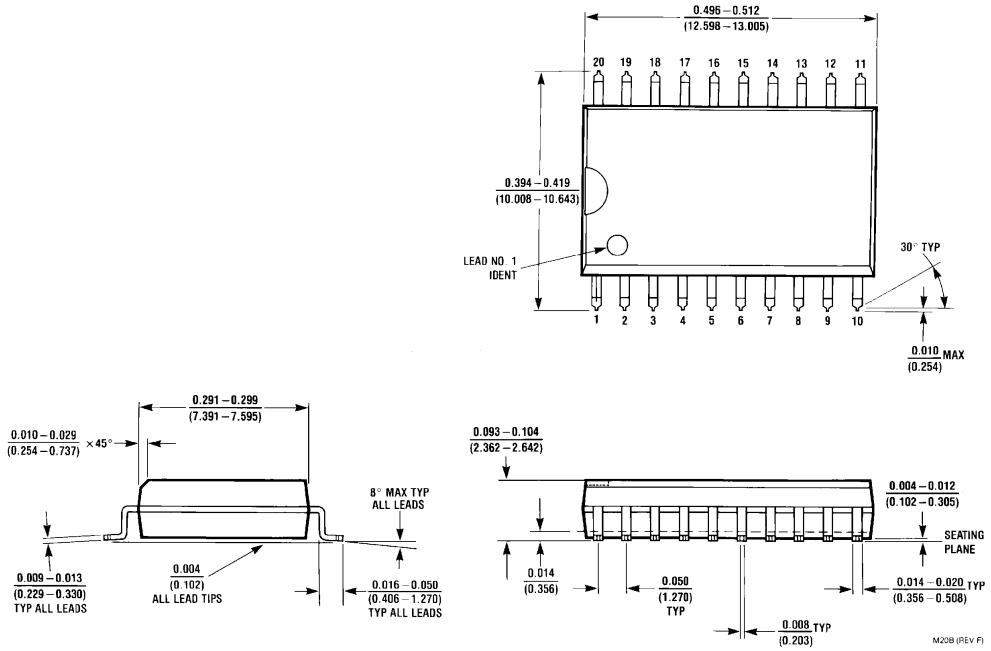


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

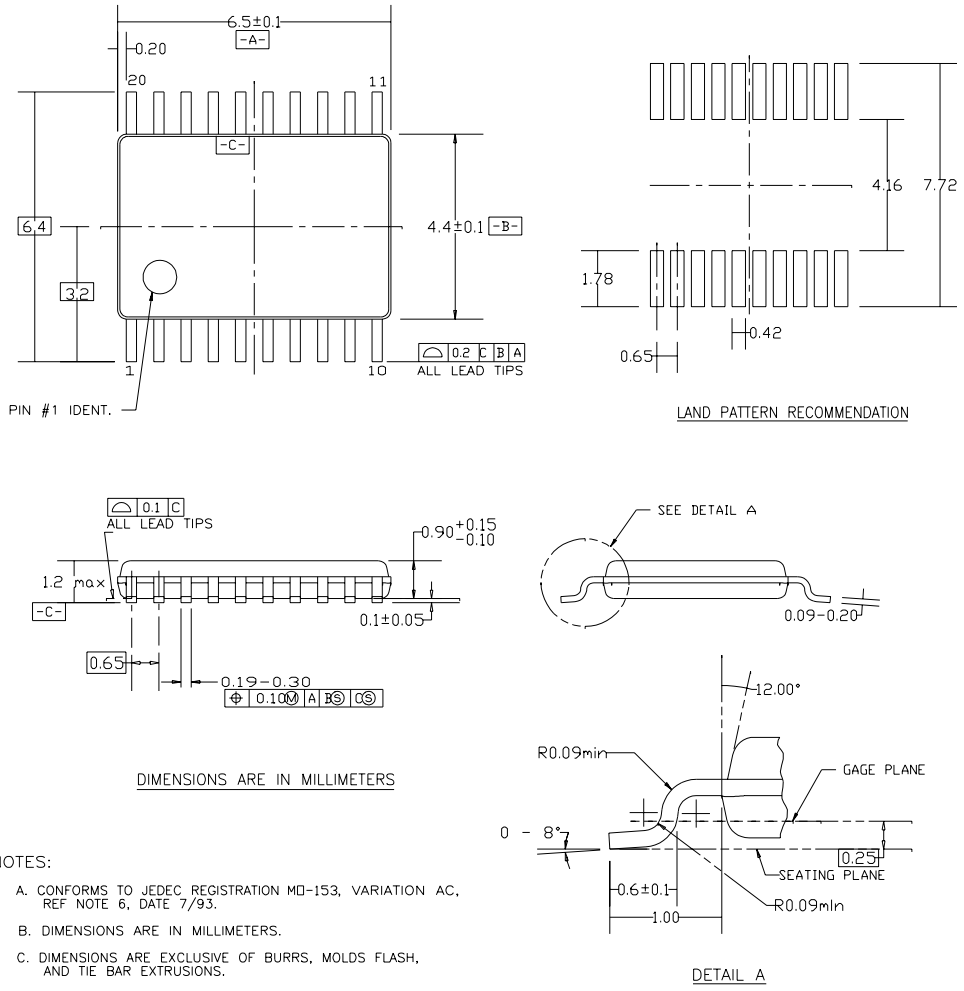
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

June 1999
Revised June 1999

74VCXH245
Low Voltage Bidirectional Transceiver with Bushold

General Description

The VCXH245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The T/$\overline{R}$ input determines the direction of data flow. The $\overline{OE}$ input disables both the A and B Ports by placing them in a high impedance state. The VCXH245 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH245 is designed for low voltage (1.65V to 3.6V) V_{CC} applications.

The 74VCXH245 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

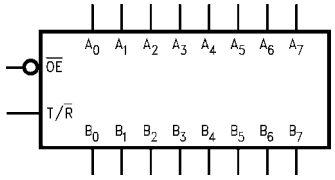
- 1.65V-3.6V V_{CC} supply operation
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- t_{PD}
  - 3.5 ns max for 3.0V to 3.6V V_{CC}
  - 4.2 ns max for 2.3V to 2.7V V_{CC}
  - 8.4 ns max for 1.65V to 1.95V V_{CC}
- Static Drive (I_{OH}/I_{OL})
  - ±24 mA @ 3.0V V_{CC}
  - ±18 mA @ 2.3V V_{CC}
  - ± 6mA @ 1.65V V_{CC}
- Uses patented Quiet Series noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description
74VCXH245WM	M20B	20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300" Wide Body
74VCXH245MTC	MTC20	20-Lead Thin Shrink Small Outline Package, JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

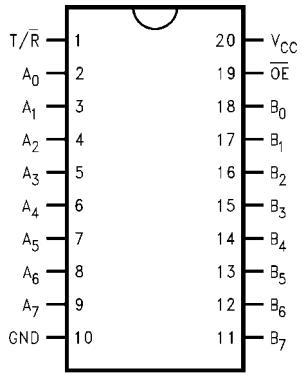


Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Bushold Inputs or 3-STATE Outputs
B_0–B_7	Side B Bushold Inputs or 3-STATE Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Connection Diagram

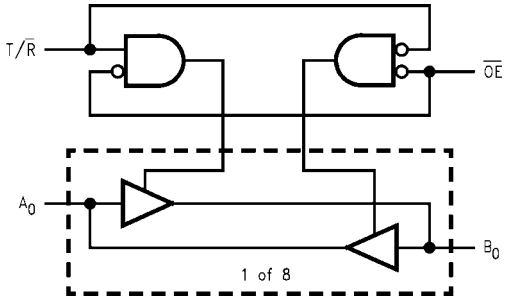


Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B_0–B_7 Data to Bus A_0–A_7
L	H	Bus A_0–A_7 Data to Bus B_0–B_7
H	X	HIGH Z State on A_0–A_7, B_0–B_7

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	
$T/\overline{R}$, $\overline{OE}$	−0.5V to +4.6V
I/O Ports	−0.5V to V_{CC}+ 0.5V
DC Output Voltage (V_O)(Note 2)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current	±100 mA
Storage Temperature (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.3V to 2.7V	±18 mA
V_{CC} = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		
		I_{OH} = −18 mA	3.0	2.4		
		I_{OH} = −24 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	
		I_{OL} = 18 mA	3.0		0.4	
		I_{OL} = 24 mA	3.0		0.55	
I_I	Input Leakage Current	V_{IN} = V_{CC} or GND	2.7–3.6		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Minimum	V_{IN} = 0.8V	3.0	75		µA
	Drive Hold Current	V_{IN} = 2.0V	3.0	−75		
$I_{I(OD)}$	Bushold Input Over-Drive	(Note 4)	3.6	450		µA
	Current to Change State	(Note 5)	3.6	−450		
I_{OZ}	3-STATE Output Leakage	V_O = V_{CC} or GND	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		750	µA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

DC Electrical Characteristics ($2.3V \leq V_{CC} \leq .2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.3–2.7	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.3	2.0		
		I_{OH} = −12 mA	2.3	1.8		
		I_{OH} = −18 mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.3–2.7		0.2	V
		I_{OL} = 12 mA	2.3		0.4	
		I_{OL} = 18 mA	2.3		0.6	
I_I	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	2.3–2.7		±5.0	µA
$I_{I(HOLD)}$	Bushold Imput Minimum	V_{IN} = 0.7V	2.3	45		µA
	Drive Hold Current	V_{IN} = 1.6V	2.3	−45		
$I_{I(OD)}$	Bushold Input Over-Drive	(Note 6)	2.7	300		µA
	Current to Change State	(Note 7)	2.7	−300		
I_{OZ}	3-STATE Output Leakage	$V_O = V_{CC}$ or GND	2.3–2.7		±10	µA
		$V_I = V_{IH}$ or V_{IL}				
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	µA

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

DC Electrical Characteristics ($1.65V \leq V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V_{CC}		V
V_{IL}	LOW Level Input Voltage		1.65–2.3		0.35 x V_{CC}	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	1.65–2.3	V_{CC} − 0.2		V
		I_{OH} = −6 mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	1.65–2.3		0.2	V
		I_{OL} = 6 mA	1.65		0.3	
I_I	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	1.65–2.3		±5.0	µA
$I_{I(HOLD)}$	Bushold Input Mimimum	V_{IN} = 0.57V	1.65	25		µA
	Drive Hold Current	V_{IN} = 1.07V	1.65	−25		
$I_{I(OD)}$	Bushold Input Over−Drive	(Note 8)	1.95	200		µA
	Current to Change State	(Note 9)	1.95	−200		
I_{OZ}	3-STATE Output Leakage	$V_O = V_{CC}$ or GND	1.65–2.3		±10	µA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	µA

Note 8: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 9: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics (Note 10)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay A_n to B_n or B_n to A_n	0.6	3.5	0.8	4.2	1.5	8.4	ns
t_{PZL} t_{PZH}	Output Enable Time	0.6	4.5	0.8	5.6	1.5	9.8	ns
t_{PLZ} t_{PHZ}	Output Disable Time	0.6	3.6	0.8	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 11)		0.5		0.5		0.75	ns

Note 10: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	0.3	V
			2.5	0.7	
			3.3	1.0	
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	−0.3	V
			2.5	−0.7	
			3.3	−1.0	
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8	1.3	V
			2.5	1.7	
			3.3	2.0	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
			Typical	
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	6	pF
$C_{I/O}$	Input/Output Capacitance	$V_I = 0V$ or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, $f = 10$ MHz, $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

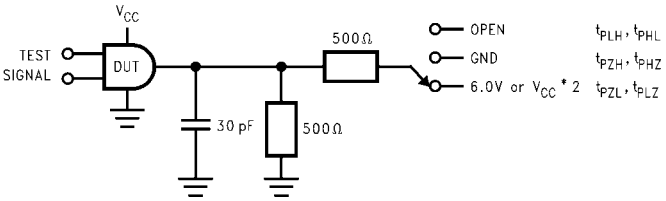


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5V ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

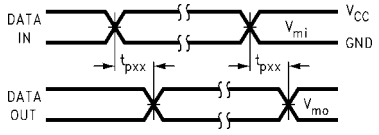


FIGURE 2. Waveform for Inverting and Non-inverting Functions

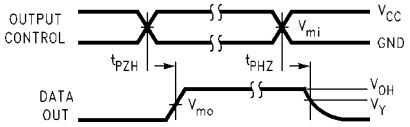


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

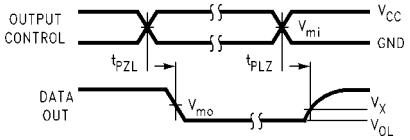
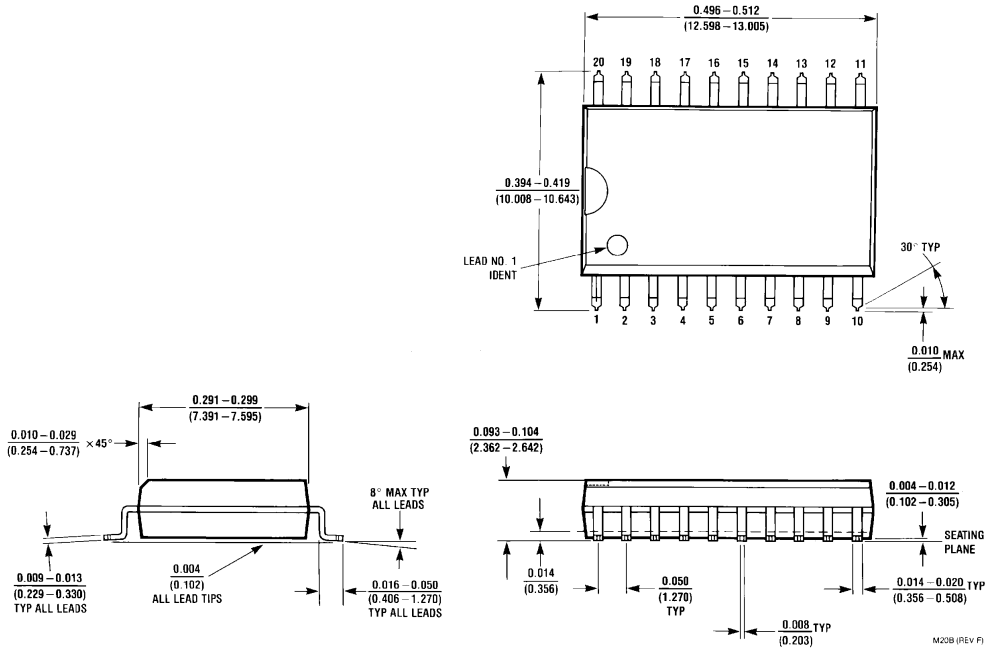


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

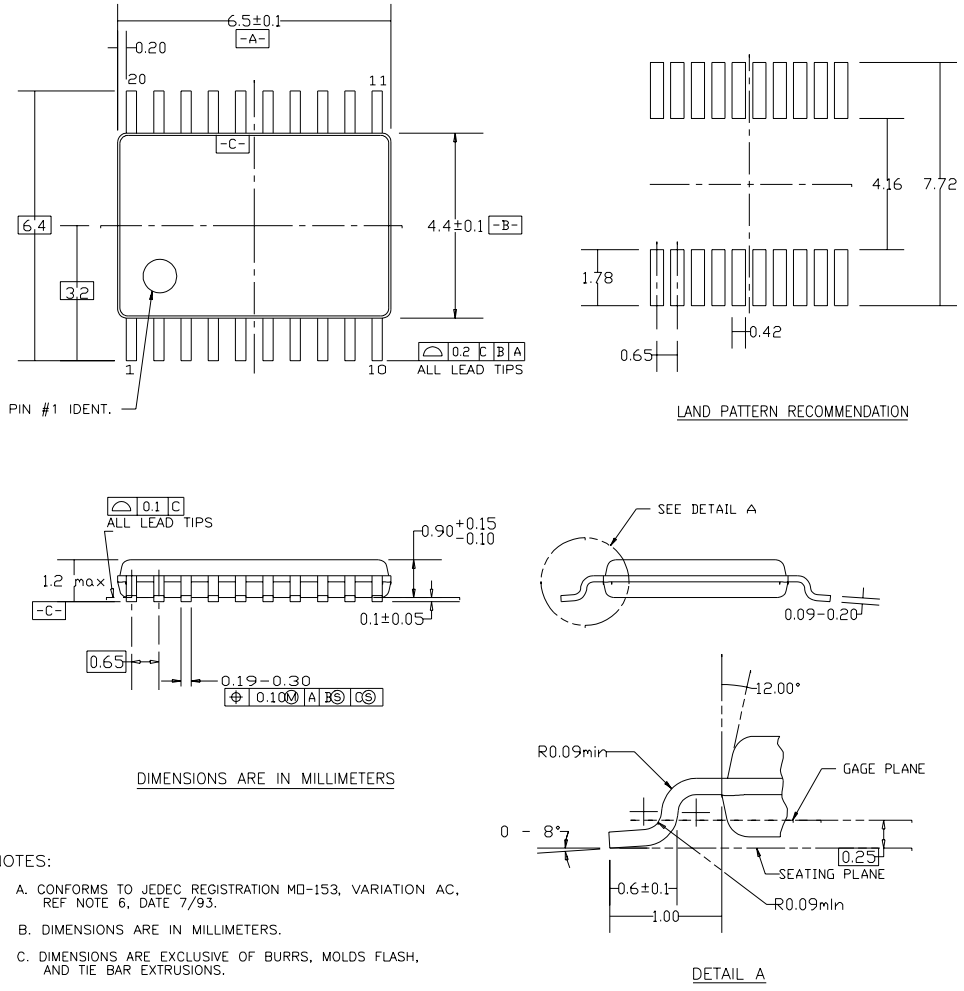
Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_x	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit, JEDEC MS-013, 0.300" Wide Body
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package, JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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August 1998
Revised April 1999

74VCXR162601

Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistors in the Outputs

General Description

The VCXR162601, 18-bit universal bus transceiver, combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable ($\overline{OEAB}$ and $\overline{OEBA}$), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable ($\overline{CLKENAB}$ and $\overline{CLKENBA}$) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH-to-LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. Output-enable $\overline{OEAB}$ is active-LOW. When $\overline{OEAB}$ is HIGH, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, LEBA, CLKBA and $\overline{CLKENBA}$.

The 74VCXR162601 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The VCXR162601 is also designed with 26Ω series resistors on both the A and B Port outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

Features

- 1.65–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors on both the A and B Port outputs.
- t_{PD} (A to B, B to A)
  - 3.8 ns max for 3.0V to 3.6V V_{CC}
  - 4.6 ns max for 2.3V to 2.7V V_{CC}
  - 9.2 ns max for 1.65V to 1.95V V_{CC}
- Power-down HIGH impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
  - ±12 mA @ 3.0V V_{CC}
  - ±8 mA @ 2.3V V_{CC}
  - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
  - Human body model > 2000V
  - Machine model >200V

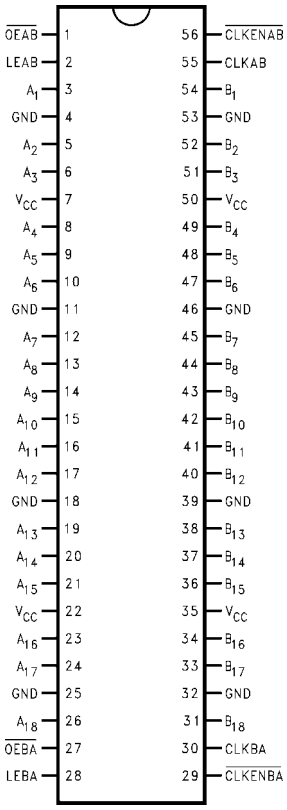
Note 1: To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCXR162601MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OEAB}$, $\overline{OEBA}$	Output Enable Inputs (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
$\overline{CLKENAB}$, $\overline{CLKENBA}$	Clock Enable Inputs
A_1–A_{18}	Side A Inputs or 3-STATE Outputs
B_1–B_{18}	Side B Inputs or 3-STATE Outputs

Function Table (Note 2)

Inputs					Outputs
$\overline{CLKENAB}$	$\overline{OEAB}$	LEAB	CLKAB	A_n	B_n
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	B_0 (Note 3)
H	L	L	X	X	B_0 (Note 3)
L	L	L	↑	L	L
L	L	L	↑	H	H
L	L	L	L	X	B_0 (Note 3)
L	L	L	H	X	B_0 (Note 4)

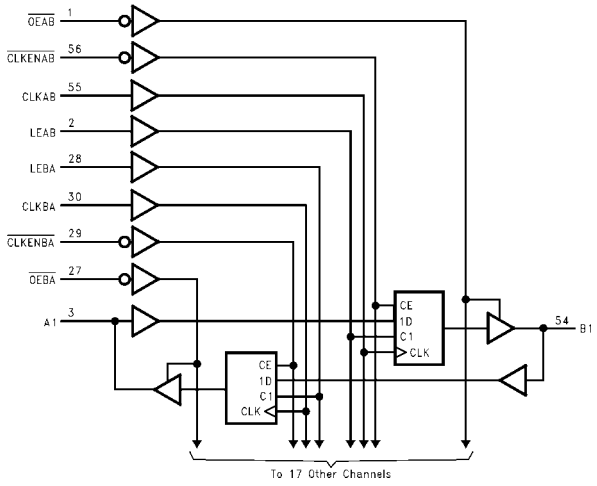
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = HIGH Impedance

Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{OEBA}$, LEBA, CLKBA, and $\overline{CLKENBA}$.

Note 3: Output level before the indicated steady-state input conditions were established

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.

Logic Diagram



Absolute Maximum Ratings (Note 5)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to +4.6V
Output Voltage (V_O)	
Outputs 3-STATE	−0.5V to +4.6V
Outputs Active (Note 6)	−0.5 to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O > V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	−0.3V to 3.6V
Output Voltage (V_O)	
Output in Active States	0V to V_{CC}
Output in 3-STATE	0.0V to 3.6V
Output Current in I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±12 mA
V_{CC} = 2.3V to 2.7V	±8 mA
V_{CC} =1.65V to 2.3V	±3 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

Note 5: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 6: I_O Absolute Maximum Rating must be observed.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −6 mA	2.7	2.2		
		I_{OH} = −8 mA	3.0	2.4		
		I_{OH} = −12 mA	3.0	2.2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 6 mA	2.7		0.4	
		I_{OL} = 8 mA	3.0		0.55	
		I_{OL} = 12 mA	3.0		0.8	
I_I	Input Leakage Current	0V ≤ V_I ≤ 3.6V	2.7–3.6		±5.0	µA
I_{OZ}	3-STATE Output Leakage	0V ≤ V_O ≤ 3.6V	2.7–3.6		±10	µA
		V_I = V_{IH} or V_{IL}				
I_{OFF}	Power Off Leakage Current	0V ≤ (V_I, V_O) ≤ 3.6V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		20	µA
		V_{CC} ≤ (V_I, V_O) ≤ 3.6V (Note 8)	2.7–3.6		±20	
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	2.7–3.6		750	µA

Note 8: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($2.3V \le V_{CC} \le 2.7V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V_{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	2.3–2.7	$V_{CC} - 0.2$		V
		$I_{OH} = -4$ mA	2.3	2.0		
		$I_{OH} = -6$ mA	2.3	1.8		
		$I_{OH} = -8$ mA	2.3	1.7		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	2.3–2.7		0.2	V
		$I_{OL} = 6$ mA	2.3		0.4	
		$I_{OL} = 8$ mA	2.3		0.6	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3–2.7		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 9)	2.3–2.7		±20	

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics ($1.65V \le V_{CC} < 2.3V$)

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V_{IL}	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\ \mu A$	1.65 - 2.3	$V_{CC} - 0.2$		V
		$I_{OH} = -3$ mA	1.65	1.25		
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\ \mu A$	1.65 - 2.3		0.2	V
		$I_{OL} = 3$ mA	1.65		0.3	
I_I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	μA
		$V_I = V_{IH}$ or V_{IL}				
I_{OFF}	Power Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μA
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 10)	1.65 - 2.3		±20	

Note 10: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 11)

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $C_L = 30$ pF, $R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	250		200		125		MHz
t_{PHL}, t_{PLH}	Propagation Delay A to B or B to A	0.6	3.8	0.8	4.6	1.5	9.2	ns
t_{PHL}, t_{PLH}	Propagation Delay Clock to A or B	0.6	4.4	0.8	5.5	1.5	9.8	ns
t_{PHL}, t_{PLH}	Propagation Delay LEBA or LEAB to A or B	0.6	4.4	0.8	5.8	1.5	9.8	ns
t_{PZL}, t_{PZH}	Output Enable Time $\overline{OEBA}$ or $\overline{OEAB}$ to A or B	0.6	4.3	0.8	5.9	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time $\overline{OEBA}$ or $\overline{OEAB}$ to A or B	0.6	4.3	0.8	4.9	1.5	8.8	ns
t_S	Setup Time	1.5		1.5		2.5		ns
t_H	Hold Time	1.0		1.0		1.0		ns
t_W	Pulse Width	1.5		1.5		4.0		ns
t_{OSHL}, t_{OSLH}	Output to Output Skew (Note 12)		0.5		0.5		0.75	ns

Note 11: For $C_L = 50$pF, add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25°C$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.15 0.25 0.35	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	0.15 −0.25 −0.35	V
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30$ pF, $V_{IH} = V_{CC}$, $V_{IL} = 0V$	1.8 2.5 3.3	1.5 2.05 2.65	V

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$	Units
C_{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V, or 3.3V, $V_I = 0V$ or V_{CC}	6	pF
$C_{I/O}$	Output Capacitance	$V_I = 0V$, or V_{CC}, $V_{CC} = 1.8V$, 2.5V or 3.3V	7	pF
C_{PD}	Power Dissipation Capacitance	$V_I = 0V$ or V_{CC}, f = 10 MHz $V_{CC} = 1.8V$, 2.5V or 3.3V	20	pF

AC Loading and Waveforms

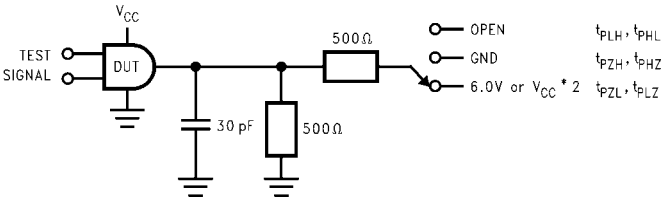


FIGURE 1. AC Test Circuit

TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V; V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t_{PZH}, t_{PHZ}	GND

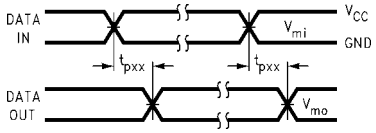


FIGURE 2. Waveform for Inverting and Non-inverting Functions

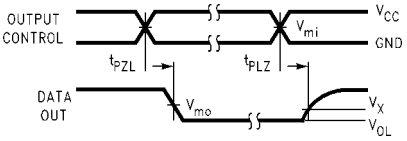


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

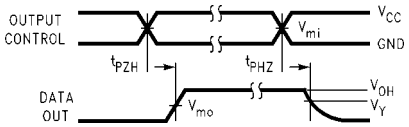


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

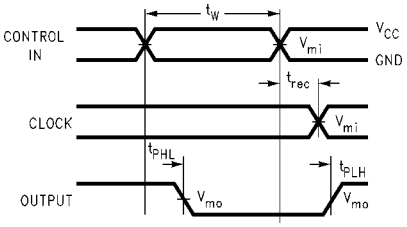


FIGURE 5. Propagation Delay, Pulse Width and t_{rec} Waveforms

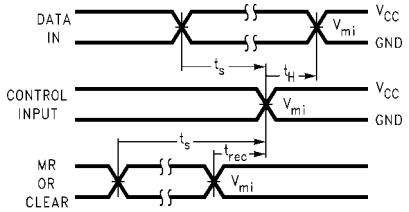
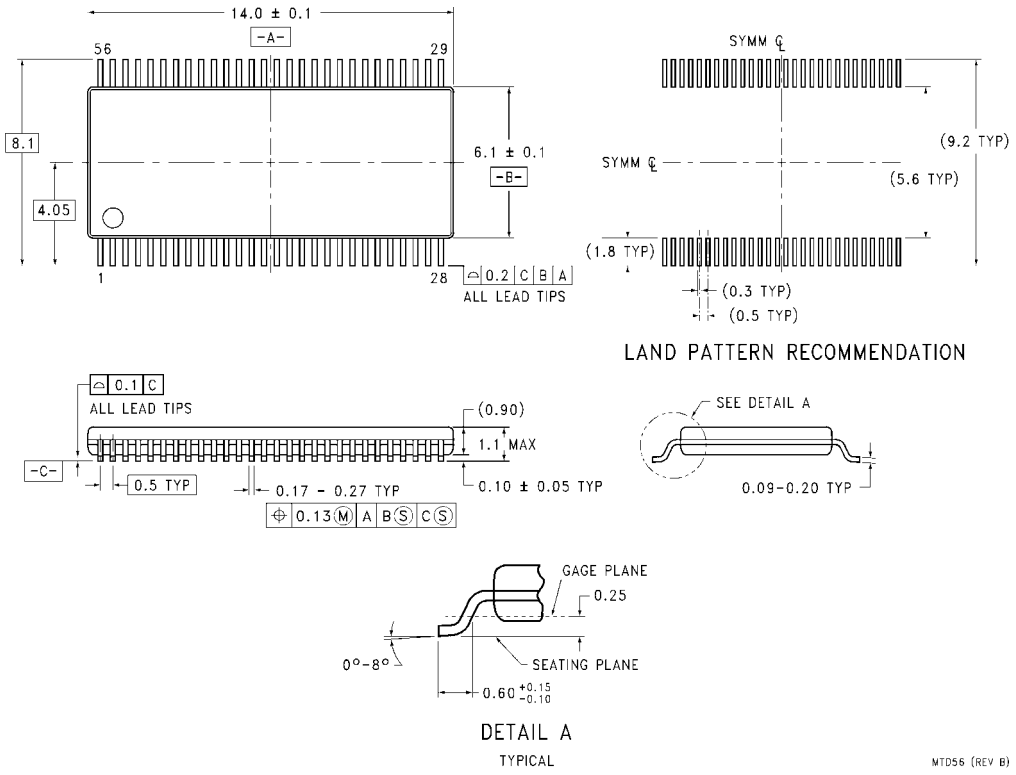


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol	V_{CC}		
	3.3V ± 0.3V	**2.5V ± 0.2V**	**1.8V ± 0.15V**
V_{mi}	1.5V	V_{CC}/2	V_{CC}/2
V_{mo}	1.5V	V_{CC}/2	V_{CC}/2
V_X	V_{OL} + 0.3V	V_{OL} + 0.15V	V_{OL} + 0.15V
V_Y	V_{OH} − 0.3V	V_{OH} − 0.15V	V_{OH} − 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

October 1992
Revised April 1999

74VHC00
Quad 2-Input NAND Gate

General Description

The VHC00 is an advanced high-speed CMOS 2-Input NAND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

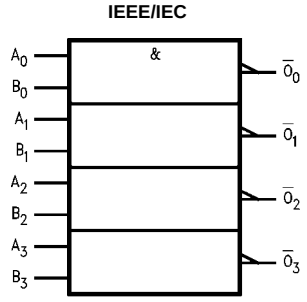
- High Speed: t_{PD} = 3.7ns (typ) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Low power dissipation: I_{CC} = 2 μA (max) at T_A = 25°C
- Pin and function compatible with 74HC00

Ordering Code:

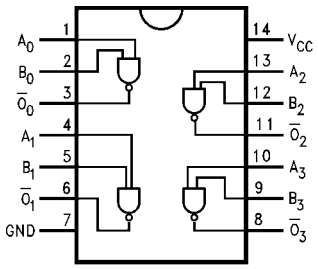
Order Number	Package Number	Package Description
74VHC00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VHC00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC00N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	B	$\overline{O}$
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} +0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.50		0.50	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9			or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4mA
		4.5	3.94			3.80				I_{OH} = −8mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1		or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

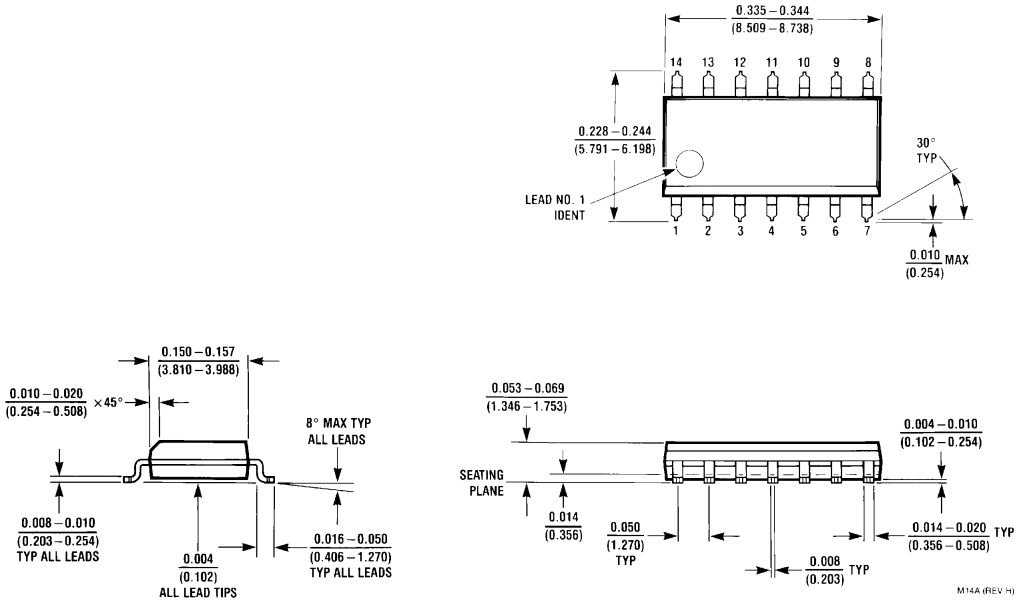
Note 3: Parameter guaranteed by design

AC Electrical Characteristics

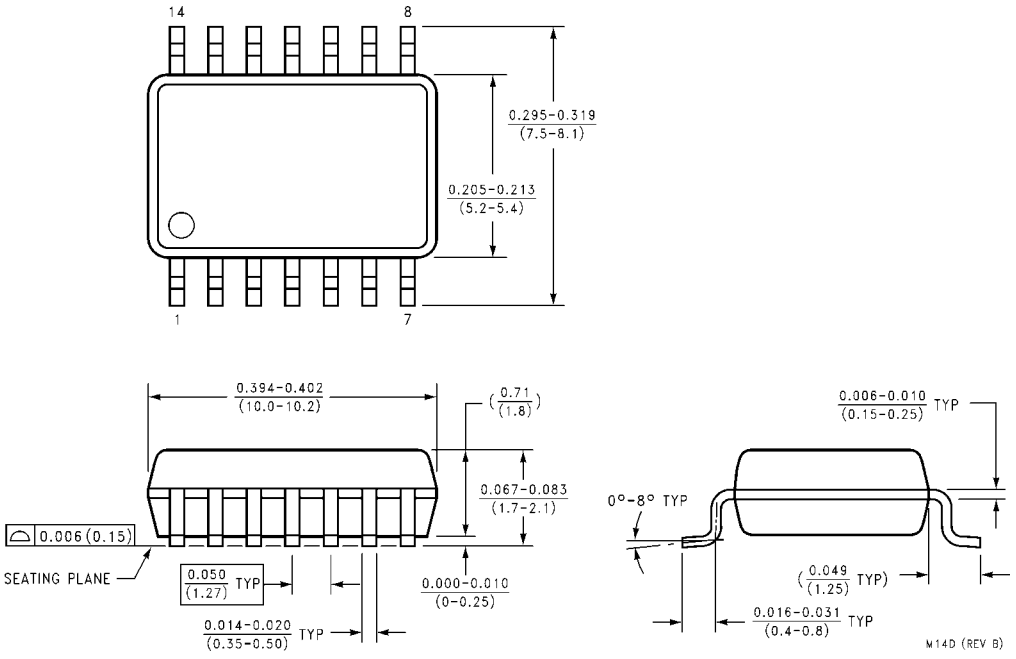
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	3.3 ± 0.3		5.5	7.9	1.0	9.5	ns	$C_L = 15$ pF
t_{PHL}	Delay			8.0	11.4	1.0	13.0		$C_L = 50$ pF
		5.0 ± 0.5		3.7	5.5	1.0	6.5	ns	$C_L = 15$ pF
				5.2	7.5	1.0	8.5		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/4$ (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

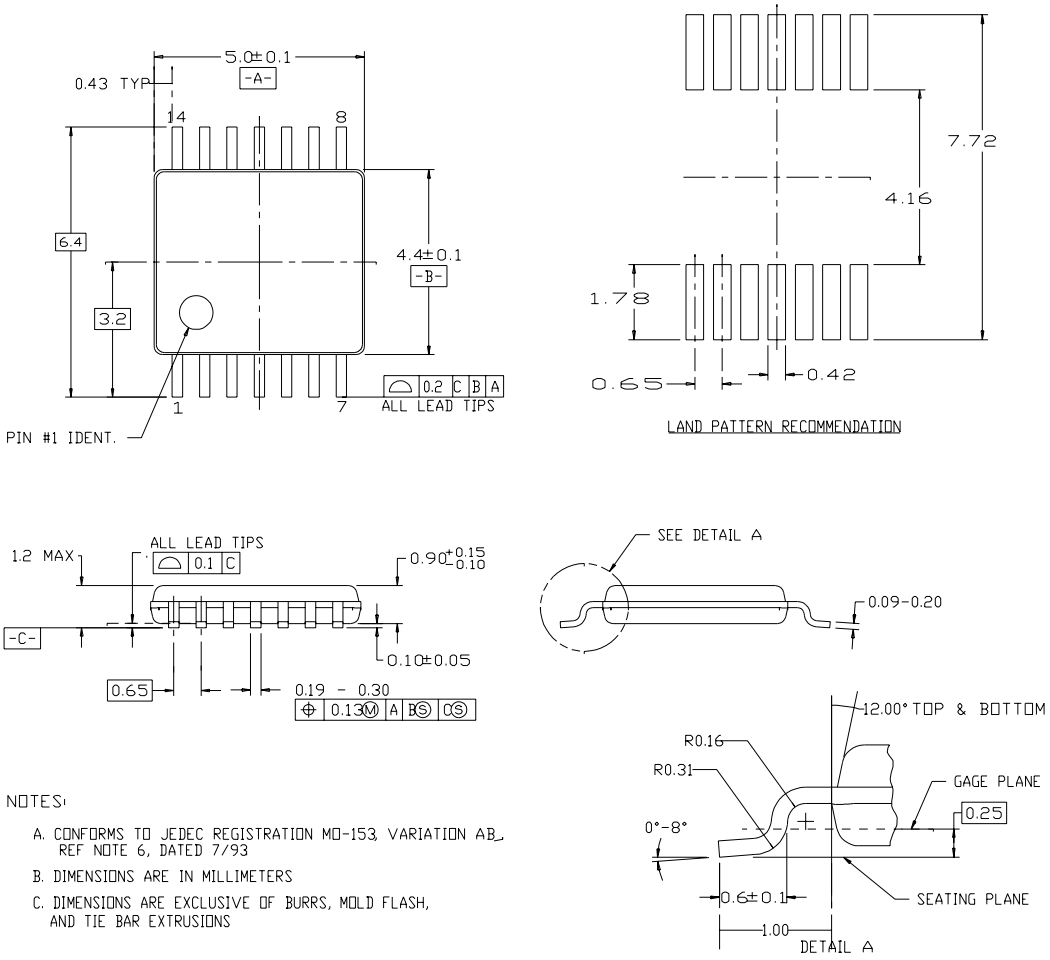


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

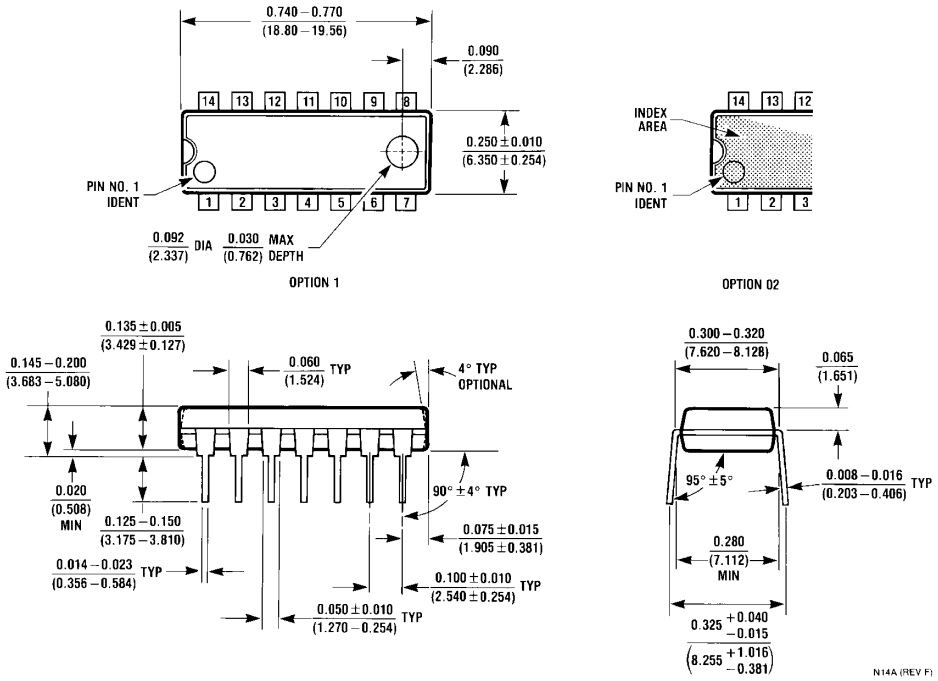
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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November 1992
Revised March 1999

74VHC02
Quad 2-Input NOR Gate

General Description

The VHC02 is an advanced high-speed CMOS 2-Input NOR Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

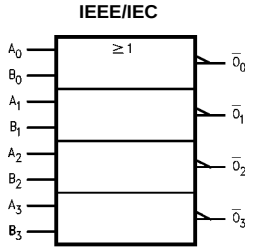
- High Speed: t_{PD} = 3.6 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 2 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC02

Ordering Code:

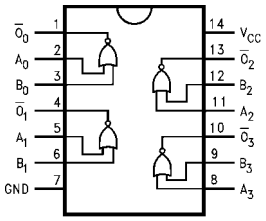
Order Number	Package Number	Package Description
74VHC02M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VHC02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC02N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	B	$\overline{O}$
L	L	H
L	H	L
H	L	L
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

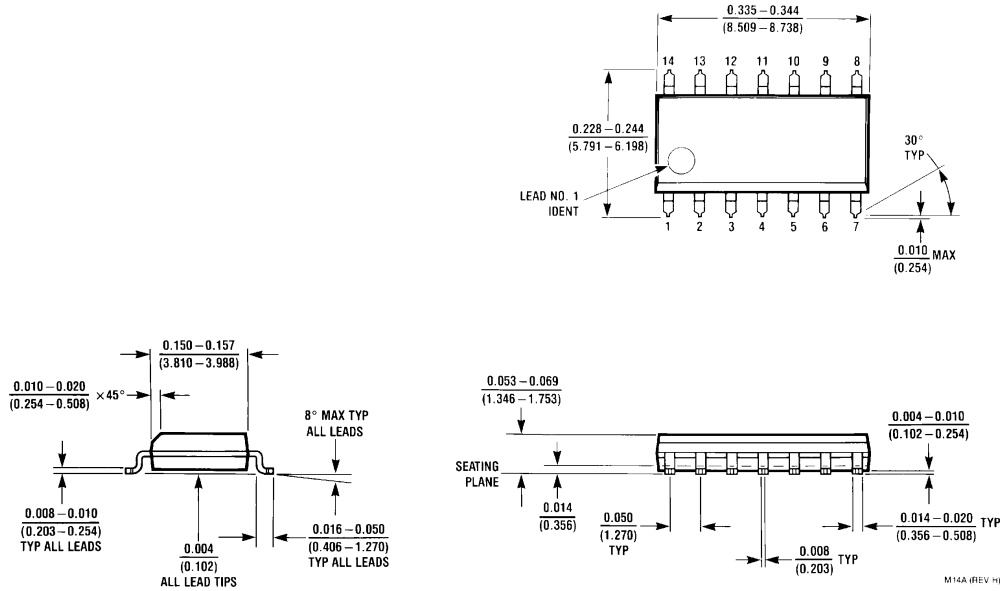
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

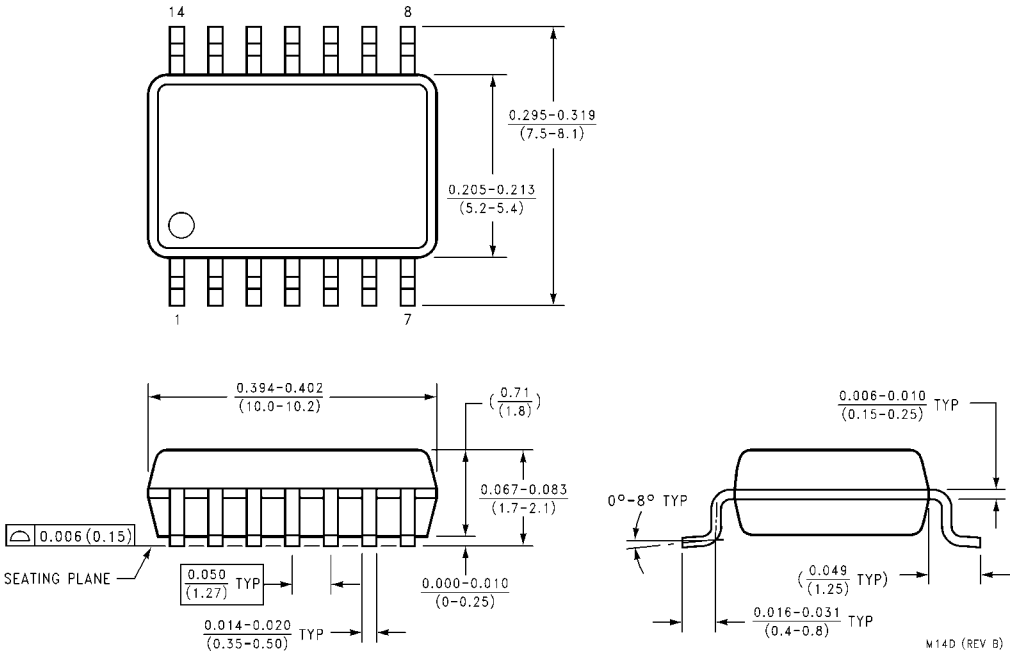
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL} t_{PLH}	Propagation Delay	3.3 ± 0.3		5.6	7.9	1.0	9.5	ns	$C_L = 15$ pF
				8.1	11.4	1.0	13.0		$C_L = 50$ pF
		5.0 ± 0.5		3.6	5.5	1.0	6.5	ns	$C_L = 15$ pF
				5.1	7.5	1.0	8.5		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			15				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

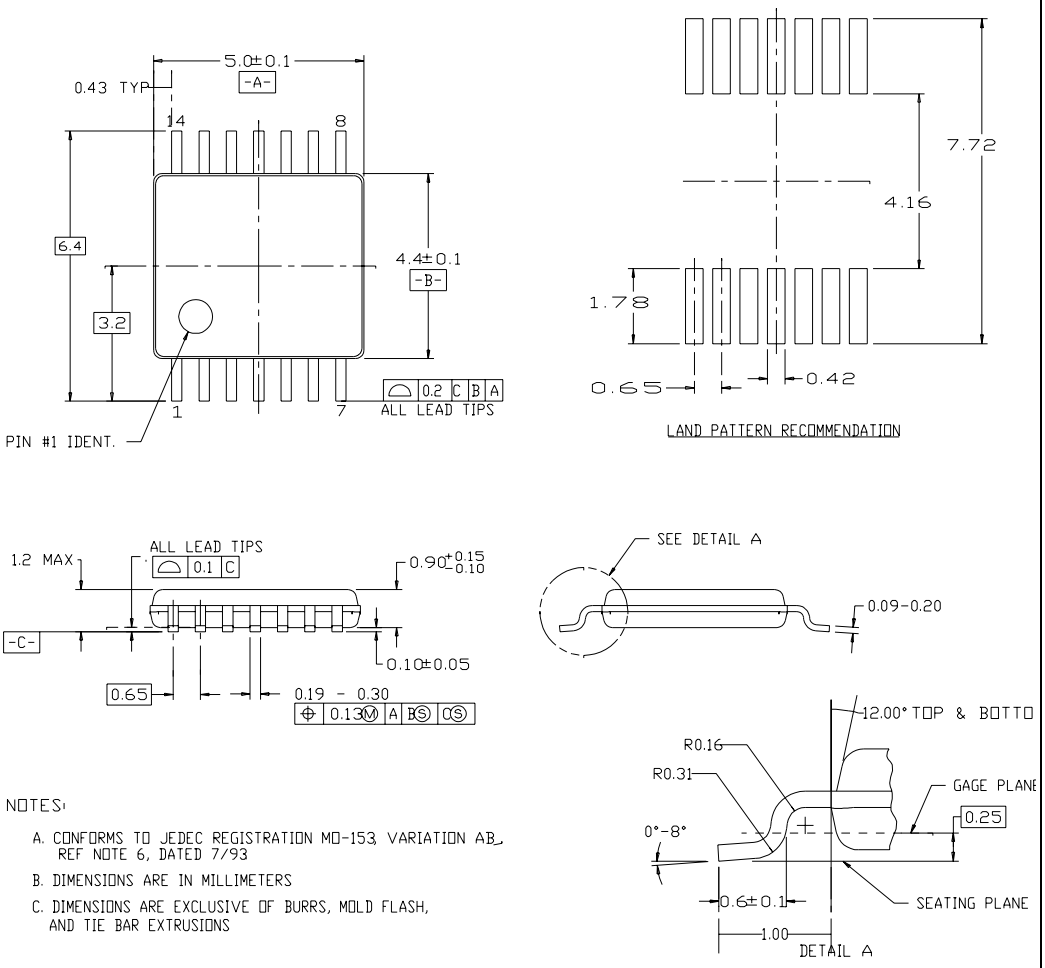


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

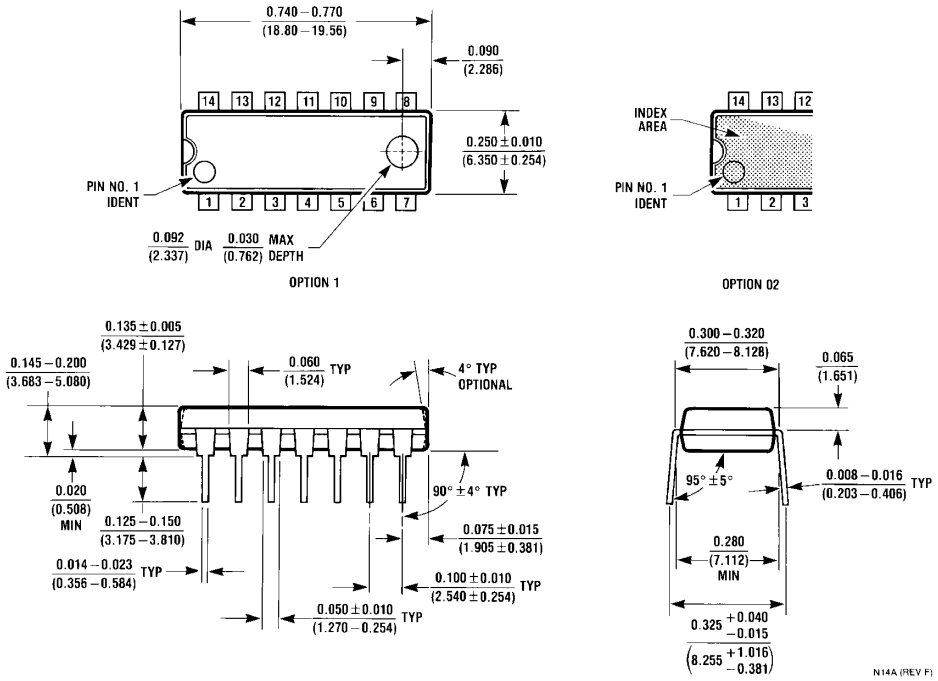
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised April 1999

74VHC04
Hex Inverter

General Description

The VHC04 is an advanced high speed CMOS Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

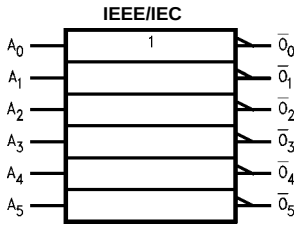
- High Speed: t_{PD} = 3.8 ns (typ) at V_{CC} = 5V
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low Noise: V_{OLP} = 0.4V (typ)
- Low power dissipation: I_{CC} = 2 μA (Max) @ T_A = 25°C
- Pin and function compatible with 74HC04

Ordering Code:

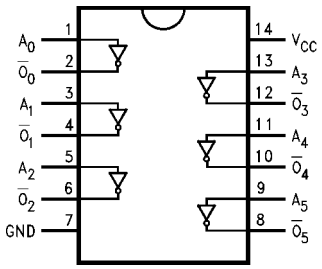
Order Number	Package Number	Package Description
74VHC04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
74VHC04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC04N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	$\overline{O}$
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = +50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

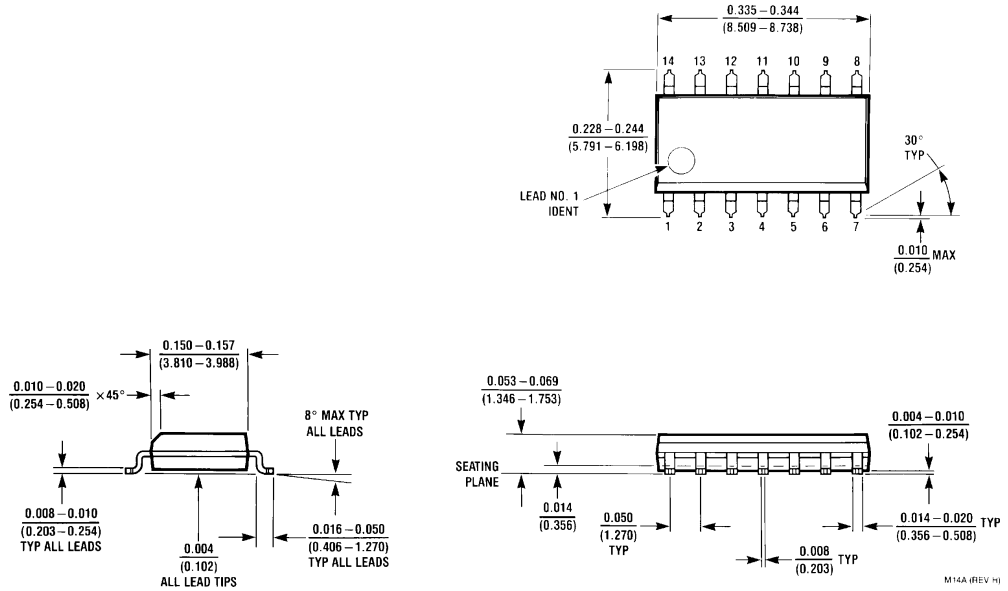
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

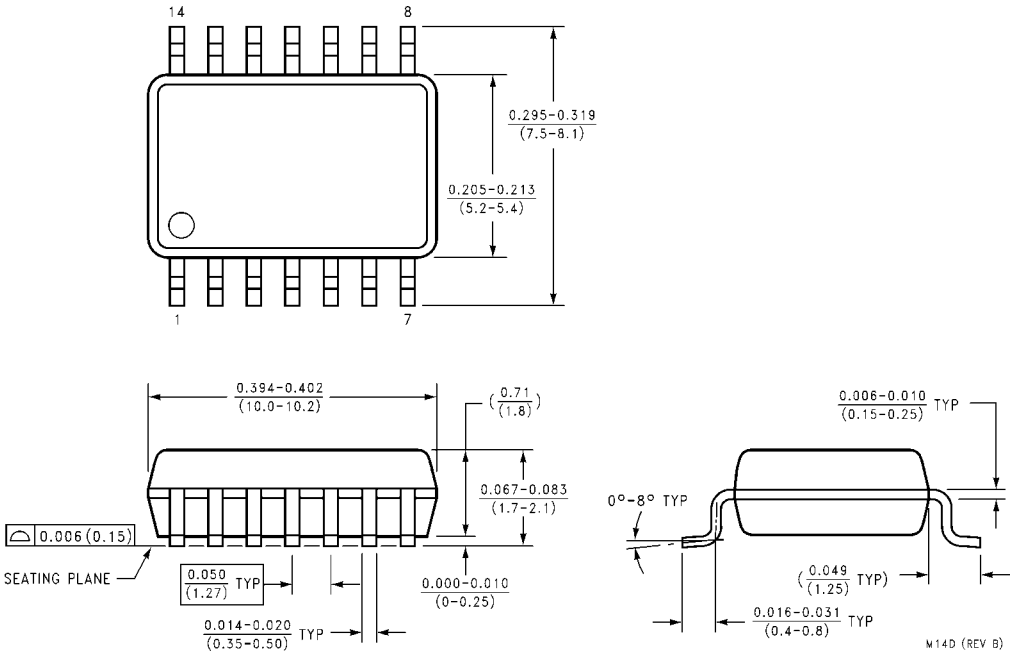
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL} t_{PLH}	Propagation Delay	3.3 ± 0.3		5.0	7.1	1.0	8.5	ns	C_L = 15 pF
				7.5	10.6	1.0	12.0		C_L = 50 pF
		5.0 ± 0.5		3.8	5.5	1.0	6.5	ns	C_L = 15 pF
				5.3	7.5	1.0	8.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/6 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

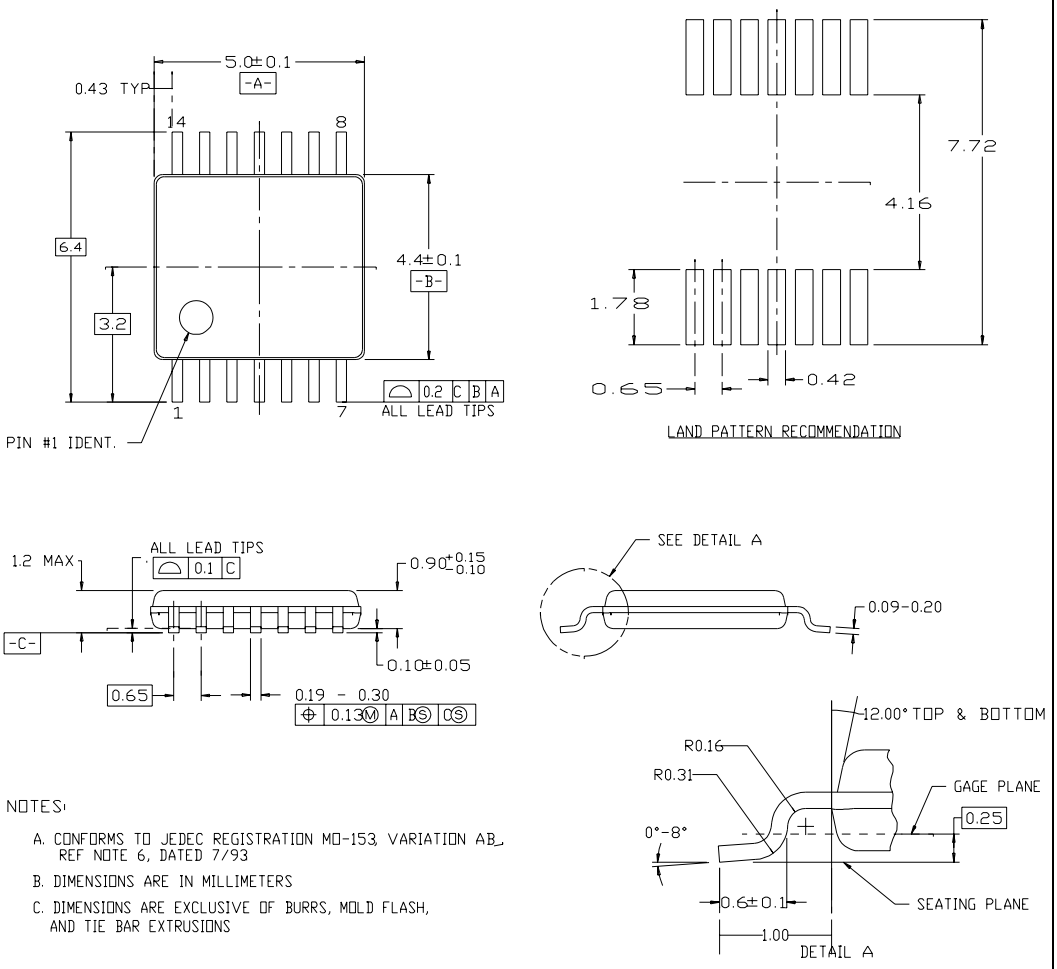


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

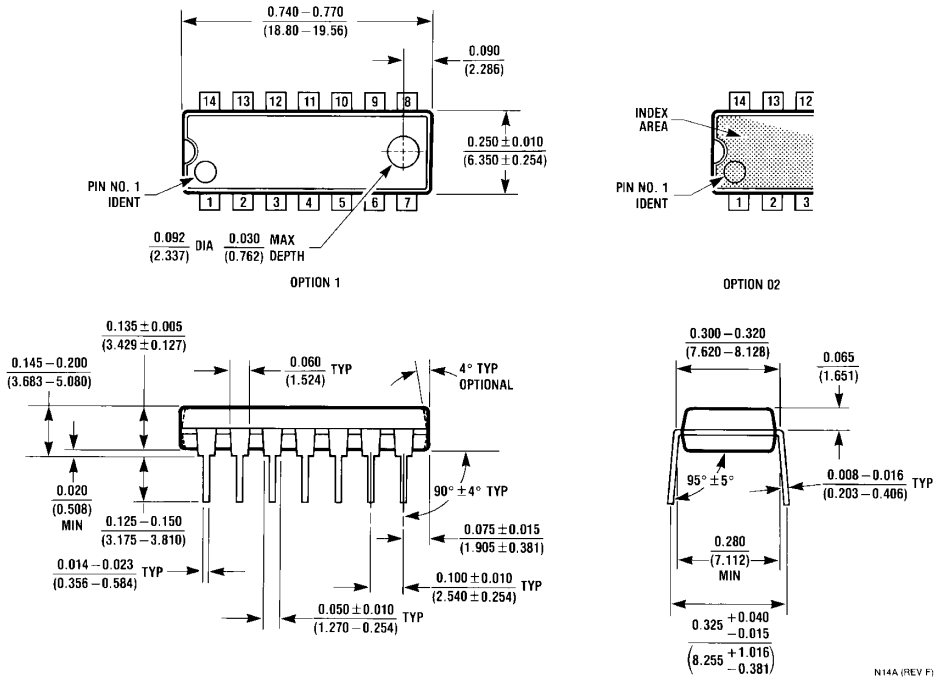
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised March 1999

74VHC08
Quad 2-Input AND Gate

General Description

The VHC08 is an advanced high speed CMOS 2 Input AND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

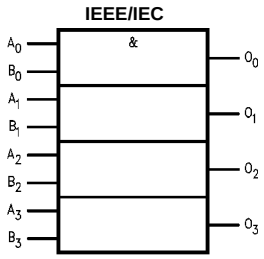
- High Speed: t_{PD} = 4.3 ns (typ) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low power dissipation: I_{CC} = 2 μA (Max) @ T_A = 25°C
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC08

Ordering Code:

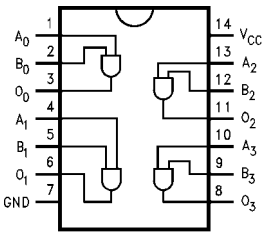
Order Number	Package Number	Package Description
74VHC08M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
74VHC08SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC08N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Truth Table

A	B	O
L	L	L
L	H	L
H	L	L
H	H	H

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 - 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 - 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

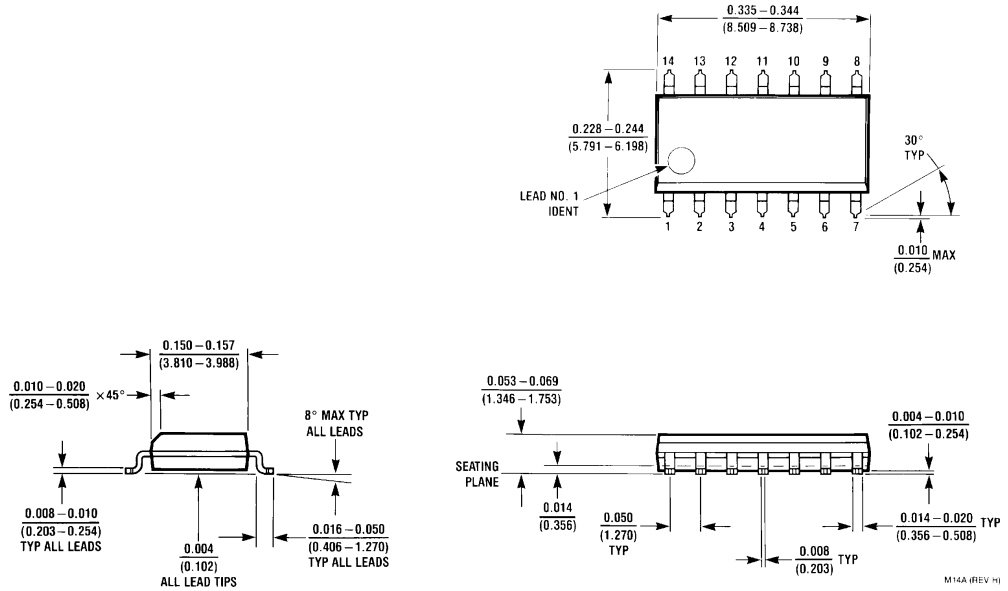
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

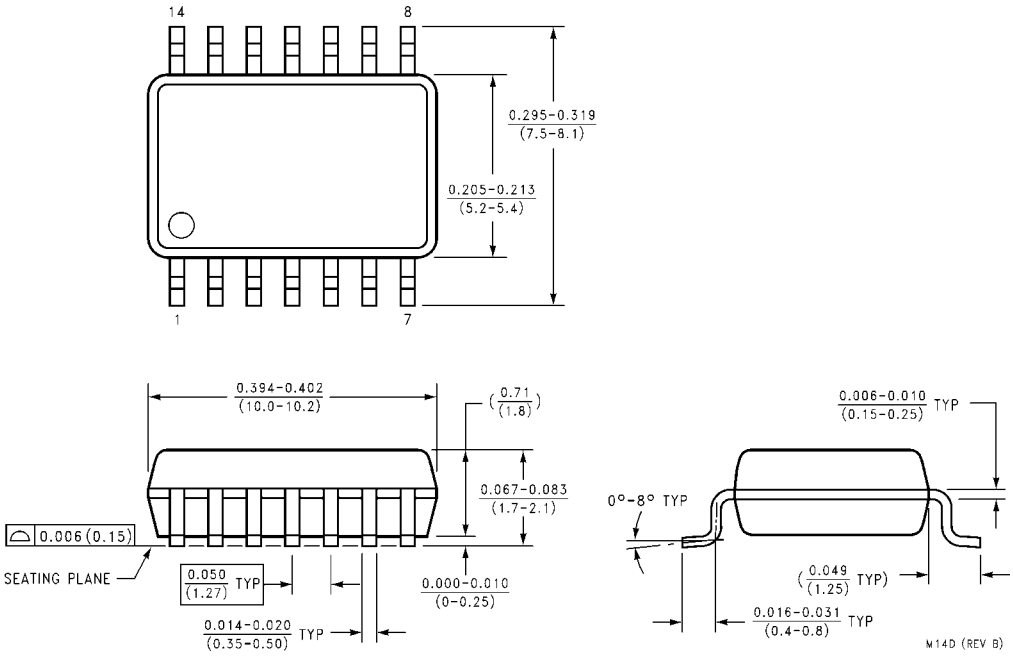
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL}	Propagation Delay	3.3 ± 0.3		6.2	8.8	1.0	10.5	ns	$C_L = 15$ pF
t_{PLH}				8.7	12.3	1.0	14.0		$C_L = 50$ pF
		5.0 ± 0.5		4.3	5.9	1.0	7.0	ns	$C_L = 15$ pF
				5.8	7.9	1.0	9.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

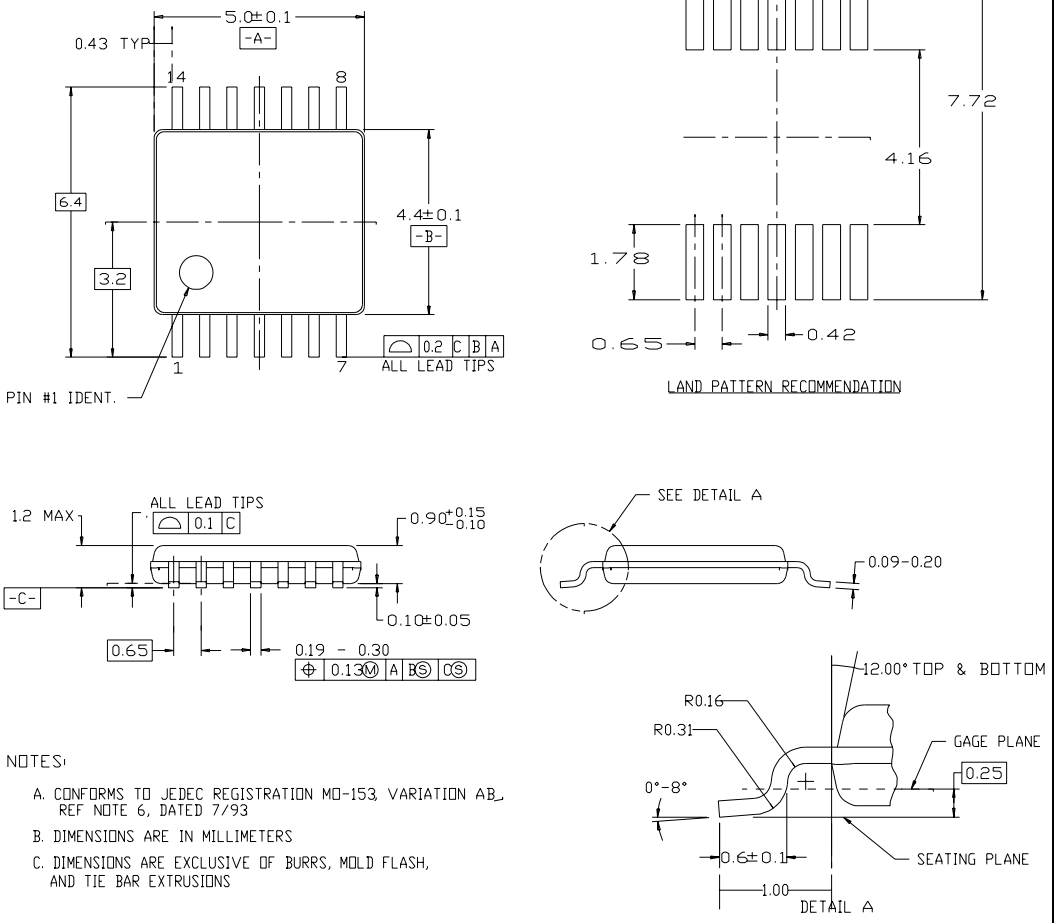


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

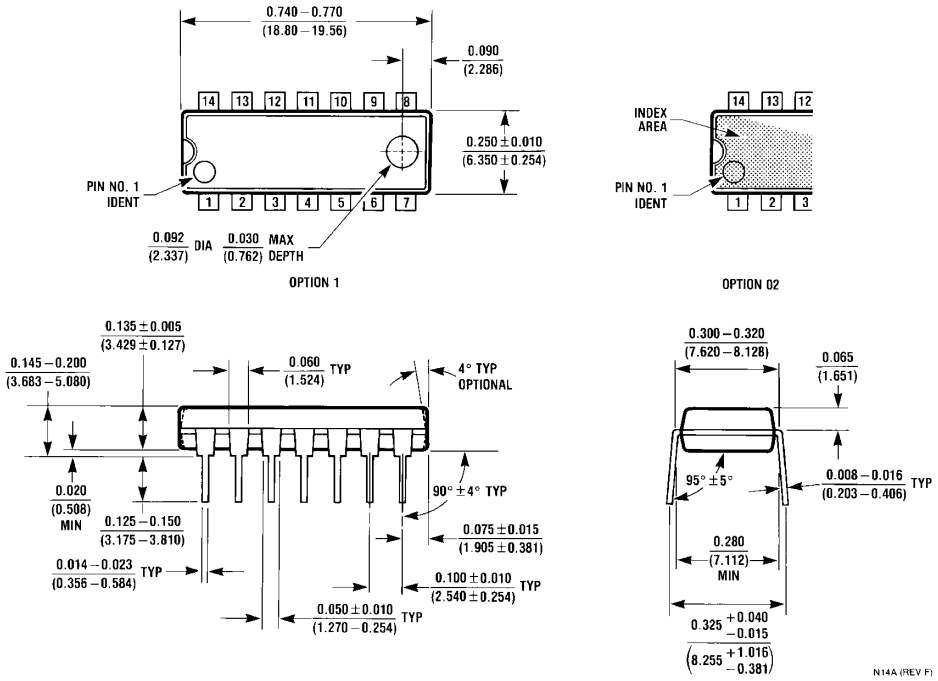
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

September 1995
Revised April 1999

74VHC112
Dual J-K Flip-Flops with Preset and Clear

General Description

The VHC112 is an advanced high speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC112 contains two independent, high-speed JK flip-flops with Direct Set and Clear inputs. Synchronous state changes are initiated by the falling edge of the clock. Triggering occurs at a voltage level of the clock and is not directly related to transition time. The J and K inputs can change when the clock is in either state without affecting the flip-flop, provided that they are in the desired state during the recommended setup and hold times relative to the falling edge of the clock. The LOW signal on PR or CLR prevents clocking and forces Q and $\overline{Q}$ HIGH, respectively.

Simultaneous LOW signals on PR and CLR force both Q and $\overline{Q}$ HIGH.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

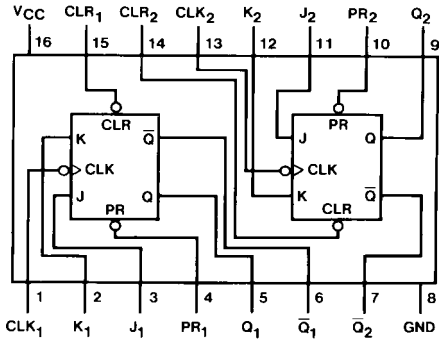
- High speed: f_{MAX} = 200 MHz (typ) at V_{CC} = 5.0V
- Low power dissipation: I_{CC} = 2 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC112

Ordering Code:

Order Number	Package Number	Package Description
74VHC112M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC112SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC112MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC112N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Descriptions

Pin Names	Description
J_1, J_2, K_1, K_2	Data Inputs
CLK_1, CLK_2	Clock Pulse Inputs (Active Falling Edge)
CLR_1, CLR_2	Direct Clear Inputs (Active LOW)
PR_1, PR_2	Direct Preset Inputs (Active LOW)
Q_1, Q_2, $\overline{Q}_1$, $\overline{Q}_2$	Outputs

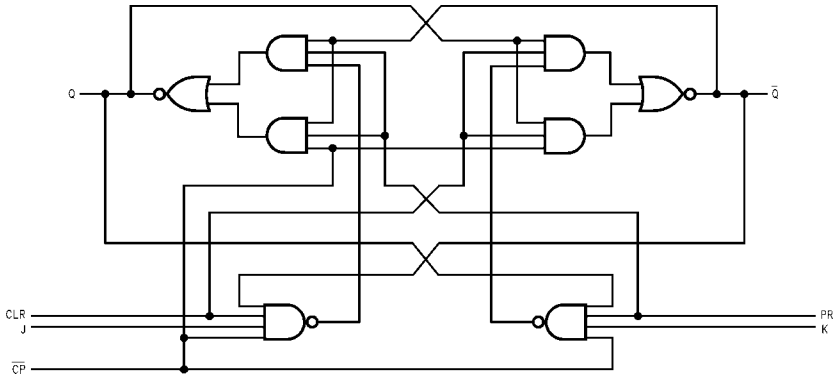
Truth Table

Inputs					Outputs	
PR	CLR	$\overline{CP}$	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	⌐	h	h	$\overline{Q}_0$	Q_0
H	H	⌐	l	h	L	H
H	H	⌐	h	l	H	L
H	H	⌐	l	l	Q_0	$\overline{Q}_0$

H (h) = HIGH Voltage Level
L (l) = LOW Voltage Level
X = Immaterial
⌐ = HIGH-to-LOW Clock Transition
Q_0 ($\overline{Q}_0$) = Before HIGH-to-LOW Transition of Clock
Lower case letters indicate the state of the referenced input or output one setup time prior to the HIGH-to-LOW clock transition.

Logic Diagram

(One Half Shown)



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.50		0.50	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
	Output Voltage	3.0	2.9	3.0		2.9			or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1		or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	110	150		100		MHz	$C_L = 15$ pF
			90	120		80			$C_L = 50$ pF
		5.0 ± 0.5	150	200		135		MHz	$C_L = 15$ pF
			120	185		110			$C_L = 50$ pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP to Q_n or $\overline{Q}_n$)	3.3 ± 0.3		8.5	11.0	1.0	13.4	ns	$C_L = 15$ pF
				10.0	15.0	1.0	16.5		$C_L = 50$ pF
		5.0 ± 0.5		5.1	7.3	1.0	8.8	ns	$C_L = 15$ pF
				6.3	10.5	1.0	12.0		$C_L = 50$ pF
t_{PLH} t_{PHL}	Propagation Delay Time (PR or CLR to Q_n or $\overline{Q}_n$)	3.3 ± 0.3		6.7	10.2	1.0	11.7	ns	$C_L = 15$ pF
				9.7	13.5	1.0	15.0		$C_L = 50$ pF
		5.0 ± 0.5		4.6	6.7	1.0	8.0	ns	$C_L = 15$ pF
				6.4	9.5	1.0	11.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 3)

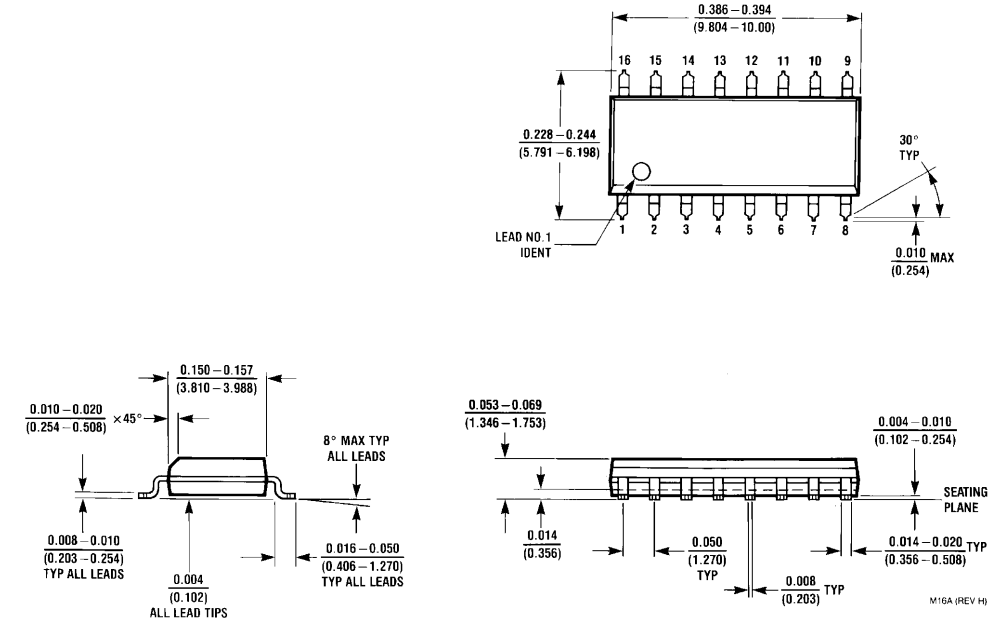
Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per F/F), and the total C_{PD} when n pcs of the Flip-Flop operate can be calculated by the following equation: C_{PD} (total) = 30 + 14 • n

AC Operating Requirements

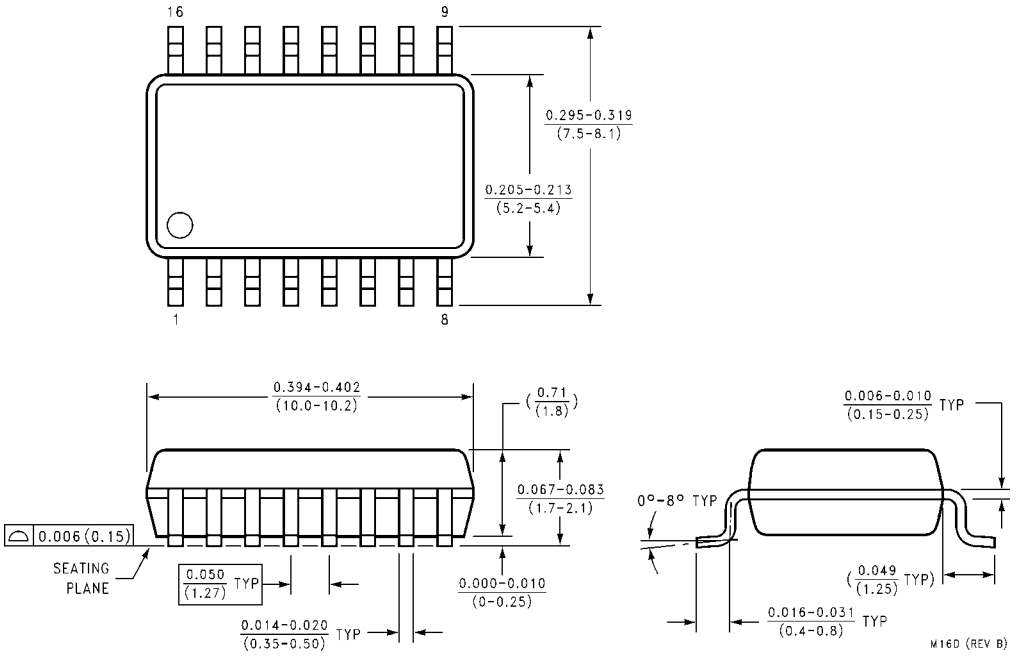
Symbol	Parameter	V_{CC} (Note 4) (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
t_W	Minimum Pulse Width	3.3		5.0	5.0	ns
	(CP or CLR or PR)	5.0		5.0	5.0	
t_S	Minimum Setup Time	3.3		5.0	5.0	ns
	(J_n or K_n to CP_n)	5.0		4.0	4.0	
t_H	Minimum Hold Time	3.3		1.0	1.0	ns
	(J_n or K_n to CP_n)	5.0		1.0	1.0	
t_{REC}	Minimum Recovery Time	3.3		6.0	6.0	ns
	(CLR or PR to CP)	5.0		5.0	5.0	

Note 4: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

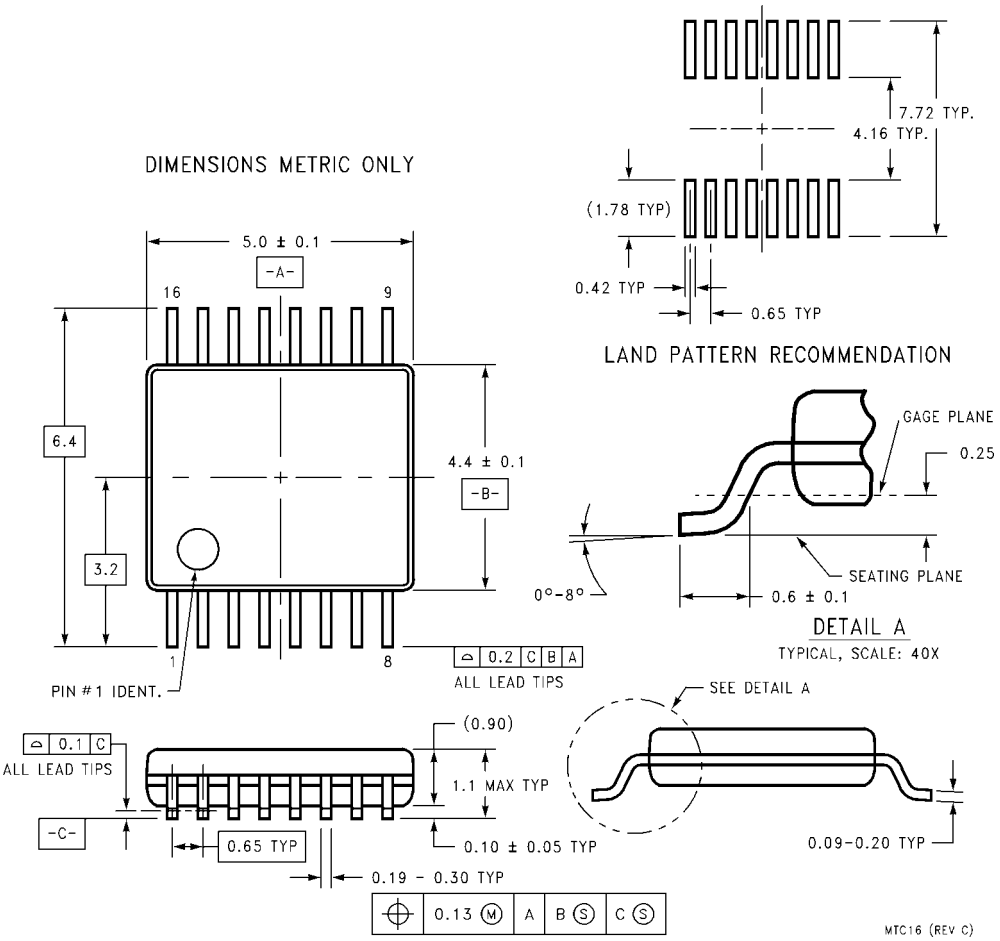


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



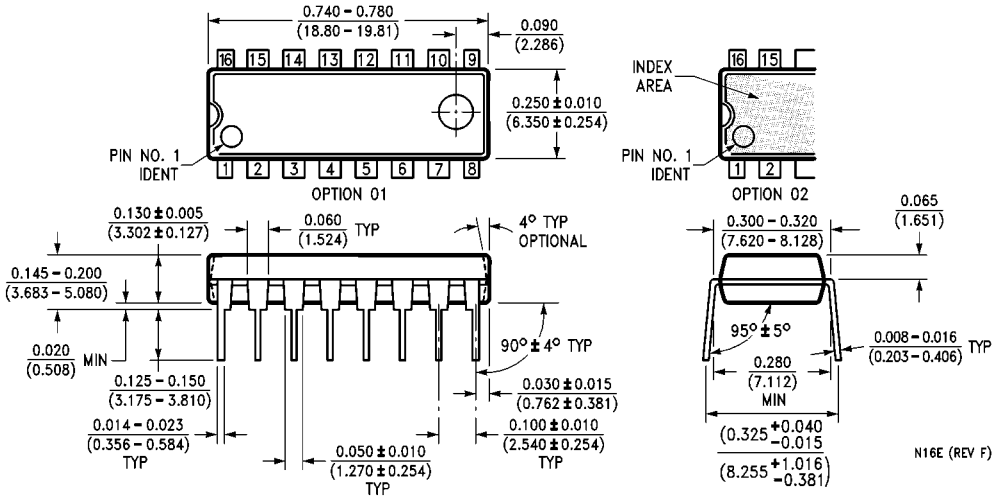
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

July 1993
Revised April 1999

74VHC123A
Dual Retriggerable Monostable Multivibrator

General Description

The VHC123A is an advanced high speed CMOS Monostable Multivibrator fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Each multivibrator features both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken low resets the one-shot. The VHC123A can be triggered on the positive transition of the clear while A is held low and B is held high. The output pulse width is determined by the equation: $PW = (R_x)(C_x)$; where PW is in seconds, R is in ohms, and C is in farads.

Limits for R_x and C_x are:

External capacitor, C_x No limit

External resistors, R_x V_{CC} = 2.0V, 5 kΩ min

V_{CC} > 3.0V, 1 kΩ min

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

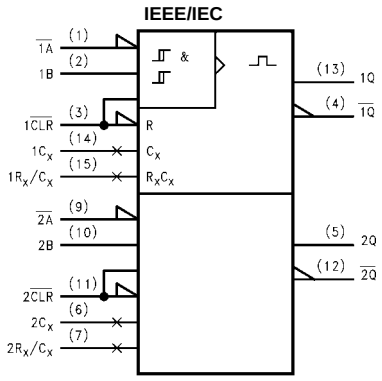
- High Speed:
  t_{PD} = 8.1 ns (typ) at T_A = 25°C
- Low Power Dissipation:
  I_{CC} = 4 μA (Max) at T_A = 25°C
- Active State: I_{CC} = 600 μA (Max) at T_A = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC123A

Ordering Code:

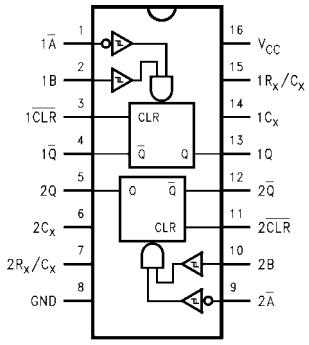
Order Number	Package Number	Package Description
74VHC123AM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150” Narrow
74VHC123ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC123AMTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC123AN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{A}$	Trigger Inputs (Negative Edge)
B	Trigger Inputs (Positive Edge)
$\overline{CLR}$	Reset Inputs
C_x	External Capacitor
R_x	External Resistor
Q, $\overline{Q}$	Outputs

Truth Table

Inputs			Outputs		Function
$\overline{A}$	B	$\overline{CLR}$	Q	$\overline{Q}$	
↓	H	H	⎍	⎍	Output Enable
X	L	H	L	H	Inhibit
H	X	H	L	H	Inhibit
L	↑	H	⎍	⎍	Output Enable
L	H	↑	⎍	⎍	Output Enable
X	X	L	L	H	Reset

H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
↓ = HIGH-to-LOW Transition
↑ = LOW-to-HIGH Transition

Block Diagrams

Note A: C_x, R_x, D_x are external Capacitor, Resistor, and Diode, respectively.

Note B: External clamping diode, D_x;

External capacitor is charged to V_{CC} level in the wait state, i.e. when no trigger is applied.

If the supply voltage is turned off, C_x discharges mainly through the internal (parasitic) diode. If C_x is sufficiently large and V_{CC} drops rapidly, there will be some possibility of damaging the IC through in rush current or latch-up. If the capacitance of the supply voltage filter is large enough and V_{CC} drops slowly, the in rush current is automatically limited and damage to the IC is avoided.

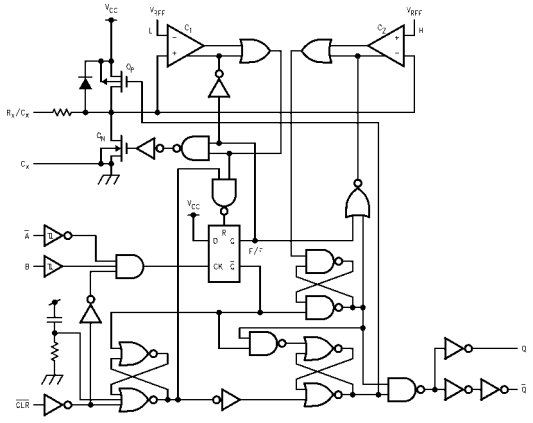
The maximum value of forward current through the parasitic diode is ±20 mA. In the case of a large Cx, the limit of fall time of the supply voltage is determined as follows:

$t_f \geq (V_{CC} - 0.7)\ C_x/20\ mA$

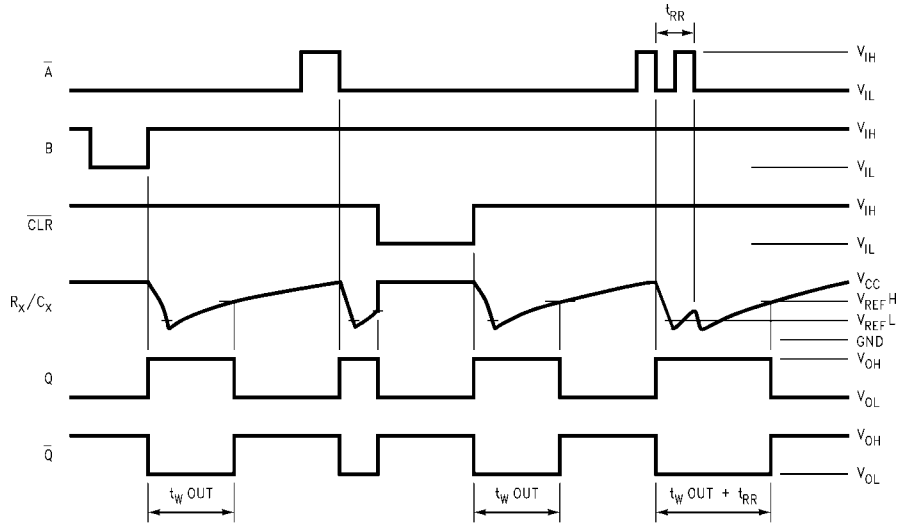
(t_f is the time between the supply voltage turn off and the supply voltage reaching 0.4 V_{CC})

In the event a system does not satisfy the above condition, an external clamping diode (D_x) is needed to protect the IC from rush current.

System Diagram



Timing Chart



Functional Description

1. Stand-by State

   The external capacitor (C_x) is fully charged to V_{CC} in the Stand-by State. That means, before triggering, the Q_P and Q_N transistors which are connected to the R_x/C_x node are in the off state. Two comparators that relate to the timing of the output pulse, and two reference voltage supplies turn off. The total supply current is only leakage current.

2. Trigger Operation

   Trigger operation is effective in any of the following three cases. First, the condition where the $\overline{A}$ input is LOW, and B input has a rising signal; second, where the B input is HIGH, and the A input has a falling signal; and third, where the $\overline{A}$ input is LOW and the B input is HIGH, and the $\overline{CLR}$ input has a rising signal.

   After a trigger becomes effective, comparators C_1 and C_2 start operating, and Q_N is turned on. The external capacitor discharges through Q_N. The voltage level at the R_x/C_x node drops. If the R_x/C_x voltage level falls to the internal reference voltage $V_{ref}L$, the output of C_1 becomes LOW. The flip-flop is then reset and Q_N turns off. At that moment C_1 stops but C_2 continues operating.

   After Q_N turns off, the voltage at the R_x/C_x node starts rising at a rate determined by the time constant of external capacitor C_x and resistor R_x.

   Upon triggering, output Q becomes HIGH, following some delay time of the internal F/F and gates. It stays HIGH even if the voltage of R_x/C_x changes from falling to rising. When R_x/C_x reaches the internal reference voltage $V_{ref}H$, the output of C_2 becomes LOW, the output Q goes LOW and C_2 stops its operation. That means, after triggering, when the voltage level of the R_x/C_x node reaches $V_{ref}H$, the IC returns to its MONOSTABLE state.

   With large values of C_x and R_x, and ignoring the discharge time of the capacitor and internal delays of the IC, the width of the output pulse, t_W (OUT), is as follows:

   t_W (OUT) = 1.0 C_x R_x

3. Retrigger operation (74VHC123A)

   When a new trigger is applied to either input $\overline{A}$ or B while in the MONOSTABLE state, it is effective only if the IC is charging C_x. The voltage level of the R_x/C_x node then falls to $V_{ref}L$ level again. Therefore the Q output stays HIGH if the next trigger comes in before the time period set by C_x and R_x.

   If the new trigger is very close to a previous trigger, such as an occurrence during the discharge cycle, it will have no effect.

   The minimum time for a trigger to be effective 2nd trigger, t_{RR} (Min), depends on V_{CC} and C_x.

4. Reset Operation

   In normal operation, the $\overline{CLR}$ input is held HIGH. If $\overline{CLR}$ is LOW, a trigger has no affect because the Q output is held LOW and the trigger control F/F is reset. Also, Q_p turns on and C_x is charged rapidly to V_{CC}.

   This means if $\overline{CLR}$ is set LOW, the IC goes into a wait state.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to 150°C
Lead Temperature (T_L)	
Soldering, 10 seconds	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature	
(T_{opr})	−40° to +85°C
Input Rise and Fall Time (t_r, t_f)	
($\overline{CLR}$ only)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V
External Capacitor - C_x	No Limitation (Note 3) F
External Resistor - R_x	>5 kΩ (Note 3) (V_{CC} = 2.0V)
	>1 kΩ (Note 3) (V_{CC} > 3.0V)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommended operation outside data book specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

Note 3: The maximum allowable values of C_x and R_x are a function of the leakage of capacitor C_x, the leakage of the device, and leakage due to board layout and surface resistance. Susceptibility to externally induced noise signals may occur for R_x> 1 MΩ.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40° to 85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.50		0.50	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44			I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{IN}	R_x/C_x Terminal	5.5			±0.25		±2.50	µA	V_{IN} = V_{CC} or GND	
	Off-State Current									
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	
I_{CC}	Active—State	3.0		160	250		280		V_{IN} = V_{CC} or GND	
	(Note 4)	4.5		380	500		650	µA	R_x/C_x = 0.5 V_{CC}	
	Supply Current	5.5		560	750		975			

Note 4: Per Circuit

AC Electrical Characteristics (Note 5)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Time (A, B–Q, $\overline{Q}$)	3.3 ± 0.3		13.4	20.6	1.0	24.0	ns	C_L = 15 pF
				15.9	24.1	1.0	27.5		C_L = 50 pF
		5.0 ± 0.5		8.1	12.0	1.0	14.0	ns	C_L = 15 pF
				9.6	14.0	1.0	16.0		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{CLR}$ Trigger—Q, $\overline{Q}$ \)	3.3 ± 0.3		14.5	22.4	1.0	26.0	ns	C_L = 15 pF
				17.0	25.9	1.0	29.5		C_L = 50 pF
		5.0 ± 0.5		8.7	12.9	1.0	15.0	ns	C_L = 15 pF
				10.2	14.9	1.0	17.0		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{CLR}$—Q, $\overline{Q}$)	3.3 ± 0.3		10.3	15.8	1.0	18.5	ns	C_L = 15 pF
				12.8	19.3	1.0	22.0		C_L = 50 pF
		5.0 ± 0.5		6.3	9.4	1.0	11.0	ns	C_L = 15 pF
				7.8	11.4	1.0	13.0		C_L = 50 pF
t_{WOUT}	Output Pulse Width	3.3 ± 0.3		160	240		300	ns	C_L = 50 pF C_x = 28 pF
		5.0 ± 0.5		133	200		240		R_x = 2 kΩ
		3.3 ± 0.3	90	100	110	90	110	µs	C_L = 50 pF C_x = 0.01 µF
		5.0 ± 0.5	90	100	110	90	110		R_x = 10 kΩ
		3.3 ± 0.3	0.9	1.0	1.1	0.9	1.1	ms	C_L = 50 pF C_x = 0.1 µF
		5.0 ± 0.5	0.9	1.0	1.1	0.9	1.1		R_x = 10 kΩ
Δt_{WOUT}	Output Pulse Width Error Between Circuits (In same Package)			±1				%	
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			73				pF	(Note 6)

Note 5: Refer to Timing Chart.

Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

I_{CC} (opr.) = C_{PD}*V_{CC}*f_{IN+} I_{CC}^{1}*Duty/100 + I_{CC}/2 (per Circuit)

I_{CC}^{1}: Active Supply Current

Duty:%

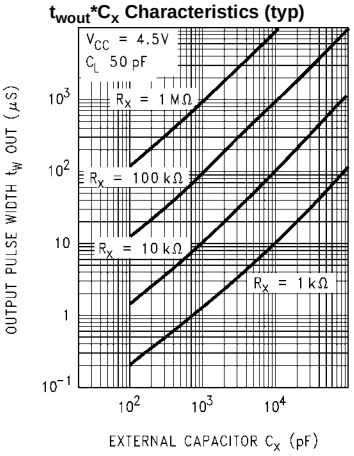
AC Operating Requirement (Note 7)

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_W(L)	Minimum Trigger	3.3		5.0			5.0	ns	
t_W(H)	Pulse Width	5.0		5.0			5.0		
t_W(L)	Minimum Clear	3.3		5.0			5.0	ns	
	Pulse Width	5.0		5.0			5.0		
t_{RR}	Minimum	3.3 ± 0.3		60				ns	R_x = 1 kΩ
	Retrigger Time	5.0 ± 0.5		39					C_X = 100 pF
		3.3		1.5				µs	R_x = 1 kΩ
		5.0		1.2					C_X = 0.01 µF

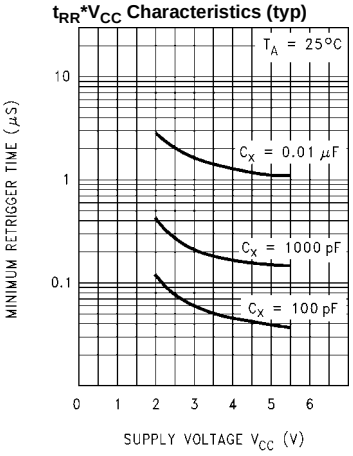
Note 7: Refer to Timing Chart.

Device Characteristics

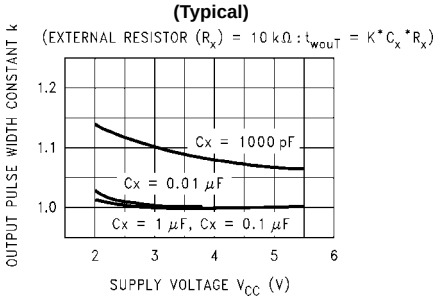
t_{wout}*C_x Characteristics (typ)



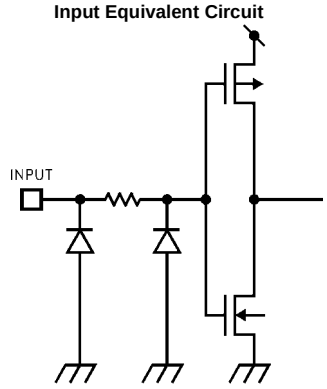
t_{RR}*V_{CC} Characteristics (typ)



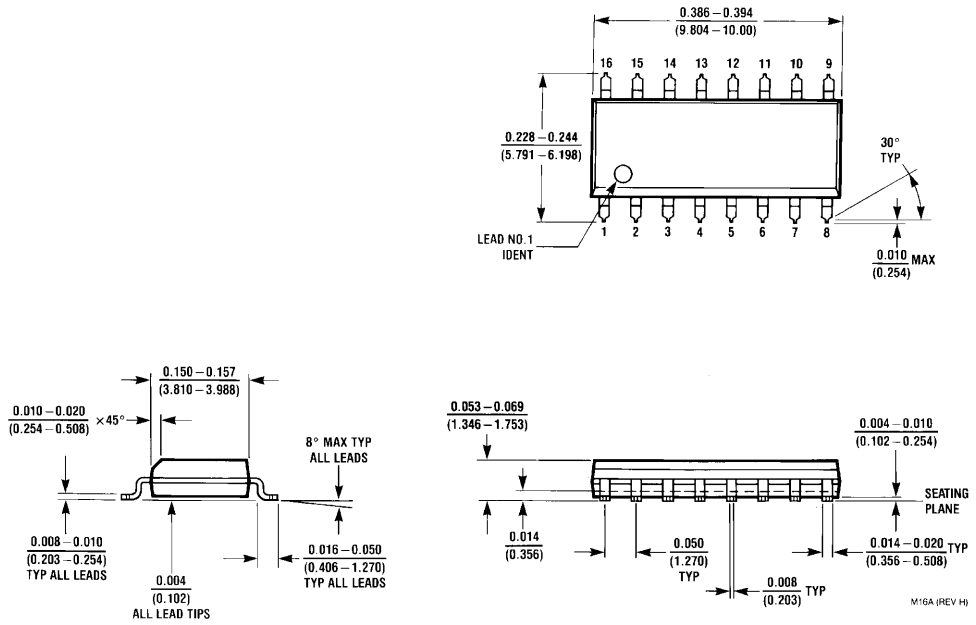
Output Pulse Width Constant K-Supply Voltage (Typical)



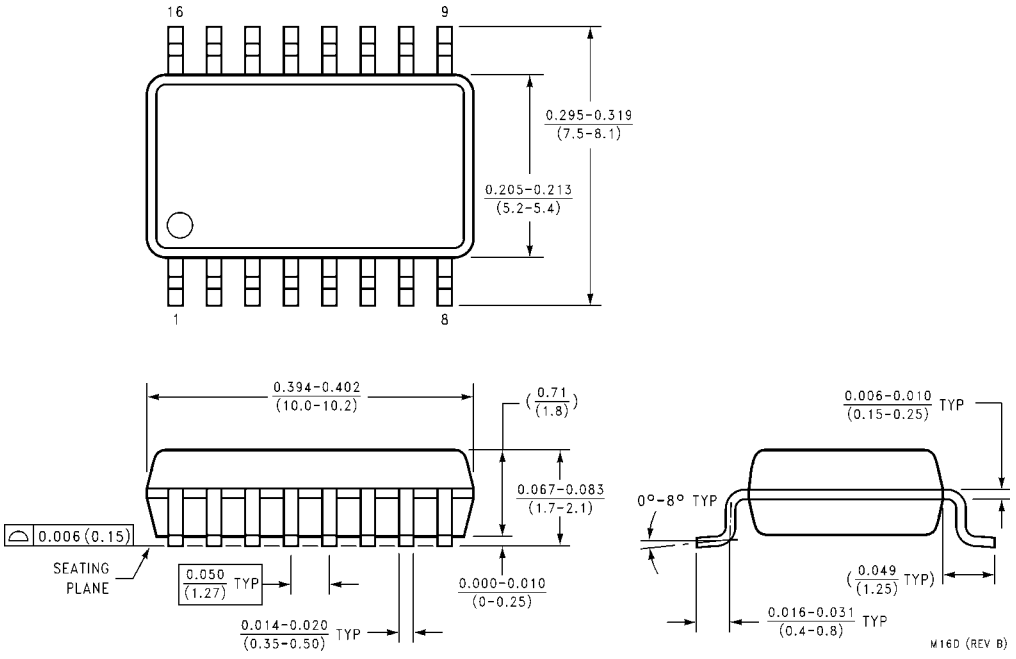
Input Equivalent Circuit



Physical Dimensions inches (millimeters) unless otherwise noted

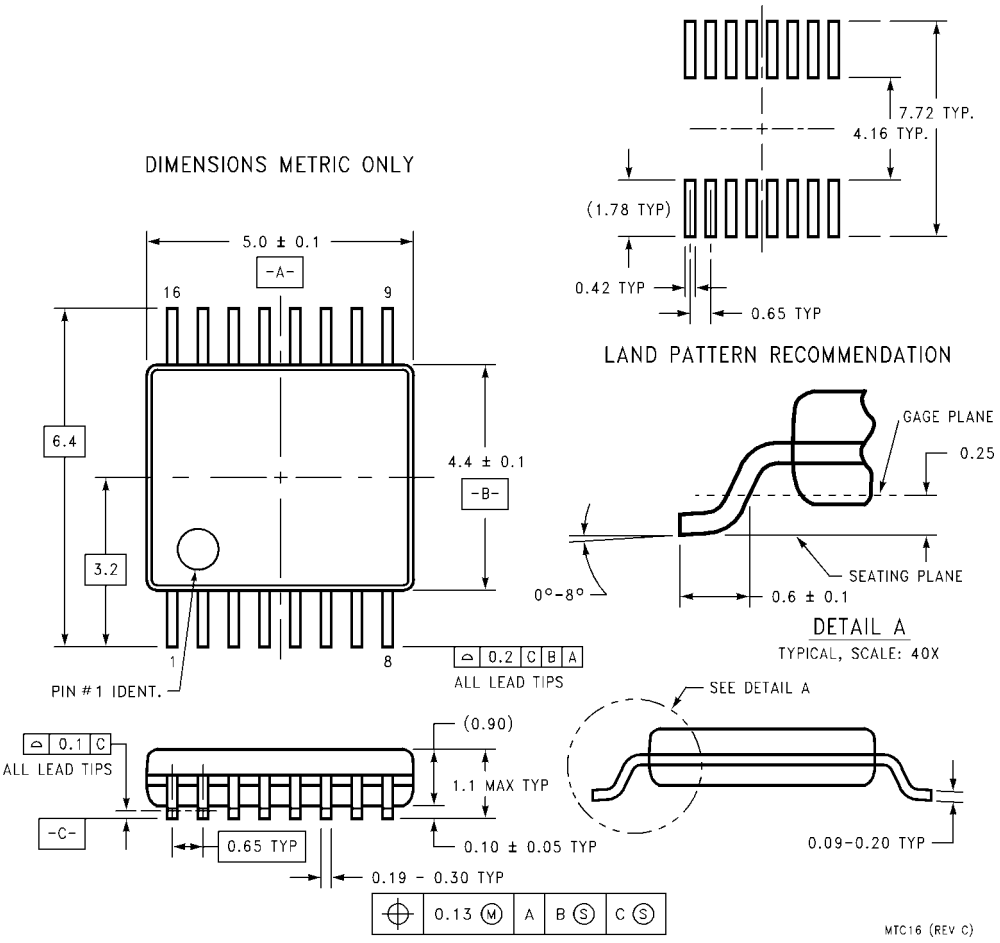


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



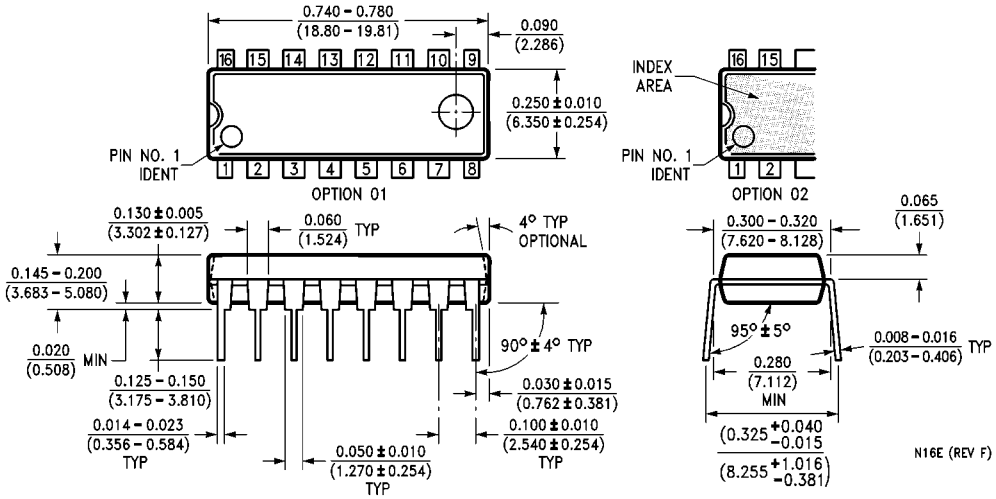
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised March 1999

74VHC125
Quad Buffer with 3-STATE Outputs

General Description

The VHC125 contains four independent non-inverting buffers with 3-STATE outputs. It is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology and achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

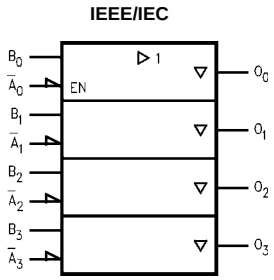
- High Speed: t_{PD} = 3.8 ns (typ) at V_{CC} = 5V
- Lower power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)

Ordering Code:

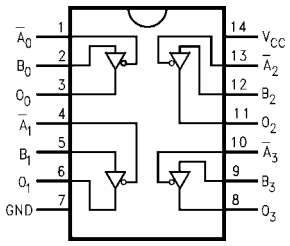
Order Number	Package Number	Package Description
74VHC125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHC125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC125N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{A}_n$, B_n	Inputs
O_n	Outputs

Function Table

Inputs		Output
$\overline{A}_n$	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
X = Immaterial

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum HIGH Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

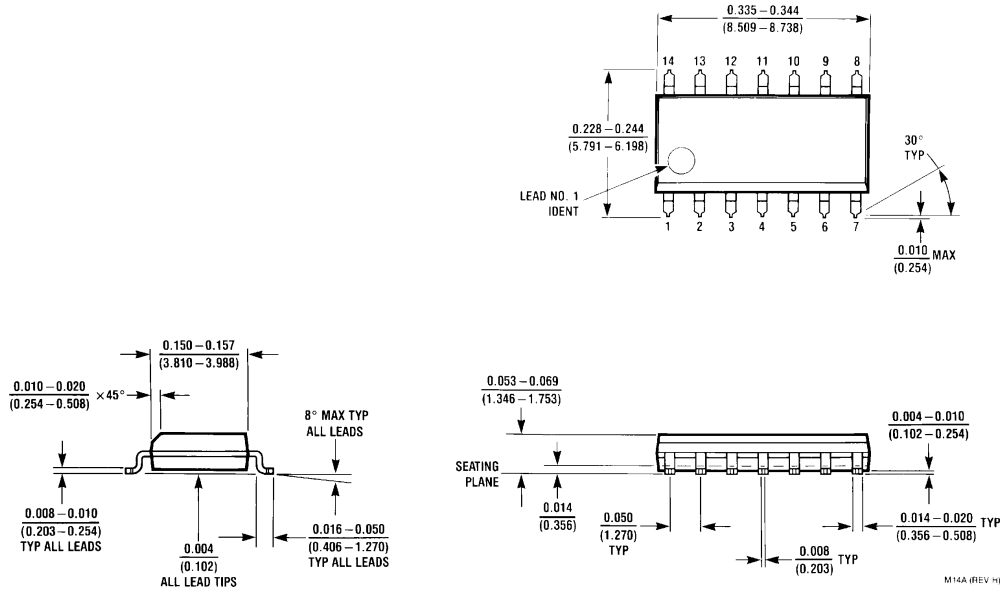
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		5.6	8.0	1.0	9.5	ns		$C_L = 15$ pF
t_{PHL}	Time			8.1	11.5	1.0	13.0			$C_L = 50$ pF
		5.0 ± 0.5		3.8	5.5	1.0	6.5	ns		$C_L = 15$ pF
				5.3	7.5	1.0	8.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		5.4	8.0	1.0	9.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			7.9	11.5	1.0	13.0			$C_L = 50$ pF
		5.0 ± 0.5		3.6	5.1	1.0	6.0	ns		$C_L = 15$ pF
				5.1	7.1	1.0	8.0			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		9.5	13.2	1.0	15.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time	5.0 ± 0.5		6.1	8.8	1.0	10.0			$C_L = 50$ pF
t_{OSLH}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	$C_L = 50$ pF
t_{OSHL}		5.0 ± 0.5			1.0		1.0			$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			14				pF	(Note 5)	

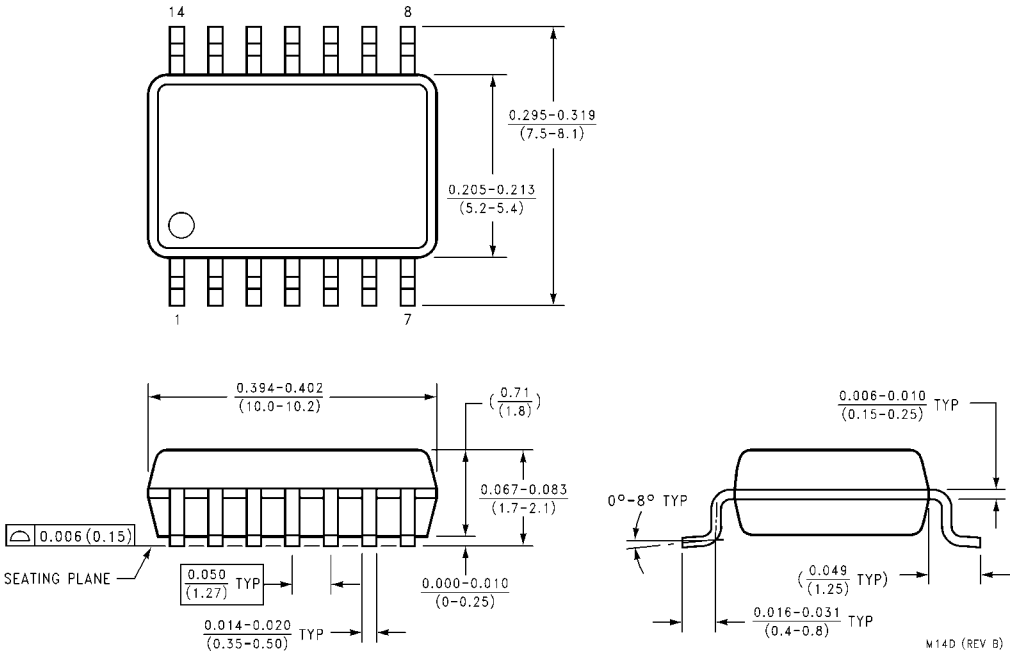
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/4$ (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

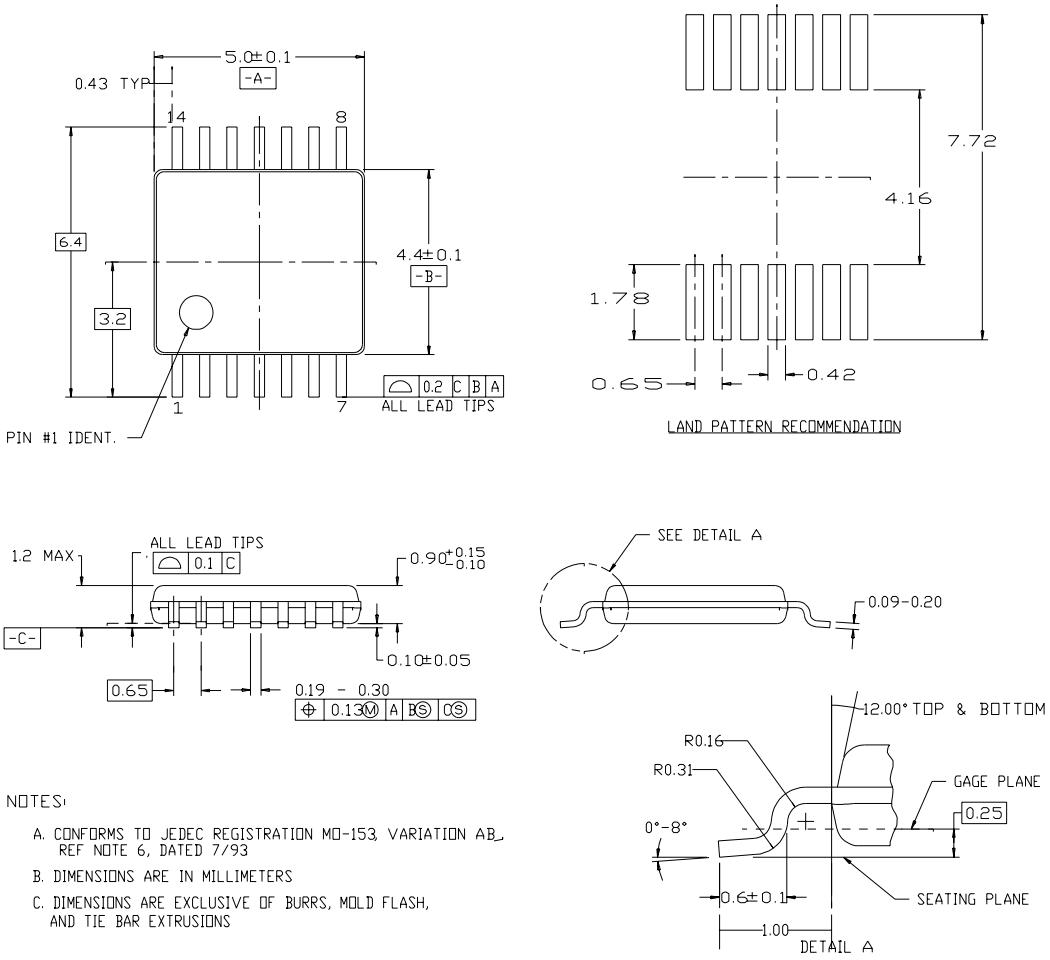


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

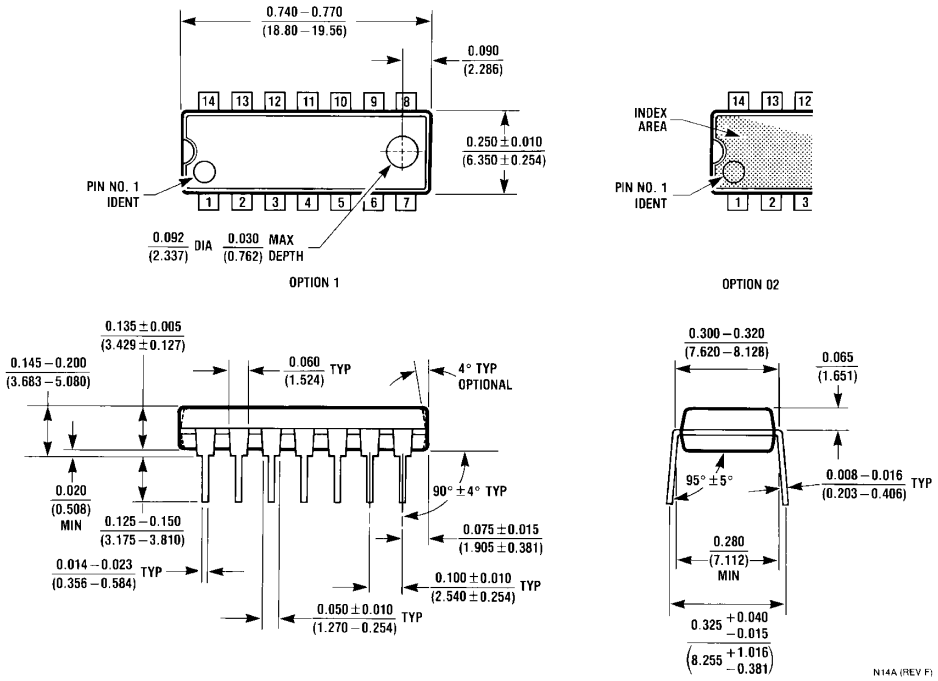
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

September 1995
Revised April 1999

74VHC132
Quad 2-Input NAND Schmitt Trigger

General Description

The VHC132 is an advanced high speed CMOS 2-input NAND Schmitt Trigger Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the VHC00 but the inputs have hysteresis between the positive-going and negative-going input thresholds, which are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. Thus greater noise margin then conventional gates is provided. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

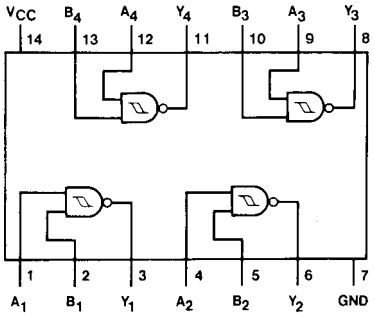
- High Speed: t_{PD} = 3.9 ns (typ) at V_{CC} = 5 V
- Power down protection is provided on all inputs
- Low power dissipation: I_{CC} = 2 μA (max) at T_A = 25°C
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74HC132

Ordering Code:

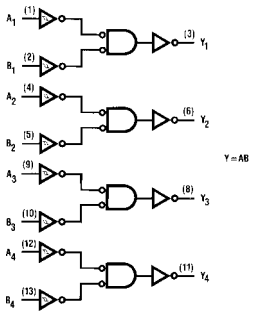
Order Number	Package Number	Package Description
74VHC132M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHC132SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC132MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC132N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
Y_n	Outputs

Truth Table

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_P	Positive	3.0			2.20		2.20			
	Threshold Voltage	4.5			3.15		3.15	V		
		5.5			3.85		3.85			
V_N	Negative	3.0	0.90			0.90				
	Threshold Voltage	4.5	1.35			1.35		V		
		5.5	1.65			1.65				
V_H	Hysteresis	3.0	0.30		1.20	0.30	1.20			
	Output Voltage	4.5	0.40		1.40	0.40	1.40	V		
		5.5	0.50		1.60	0.50	1.60			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9			V_{IN} = V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9		V	or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1		V_{IN} = V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1	V	or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	$C_L = 50$ pF
V_{OLV} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	−0.3	−0.8	V	$C_L = 50$ pF
V_{IHD} (Note 3)	Maximum HIGH Level Dynamic Input Voltage	5.0		3.5	V	$C_L = 50$ pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	$C_L = 50$ pF

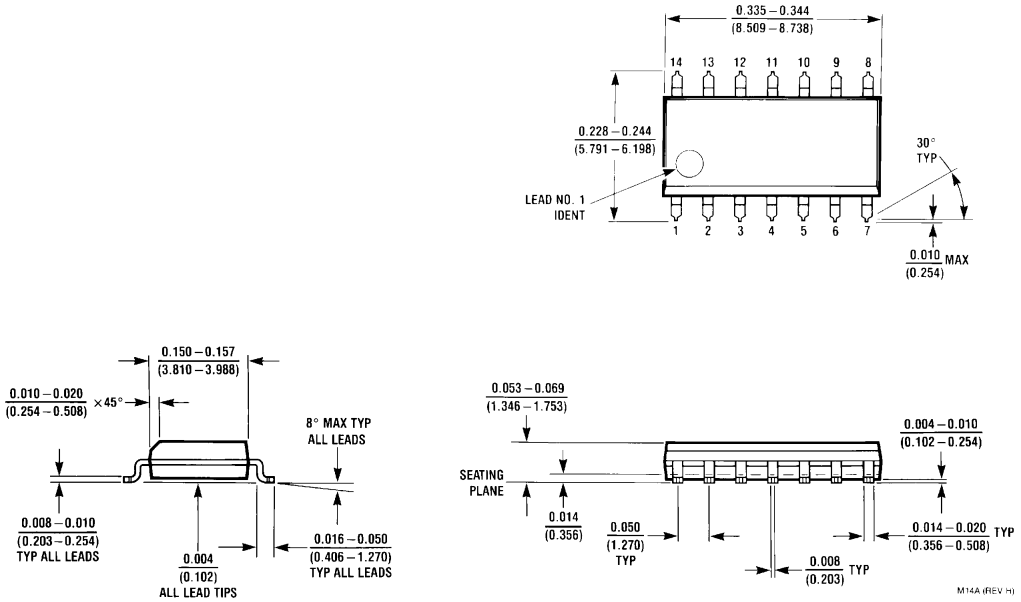
Note 3: Parameter guaranteed by design

AC Electrical Characteristics

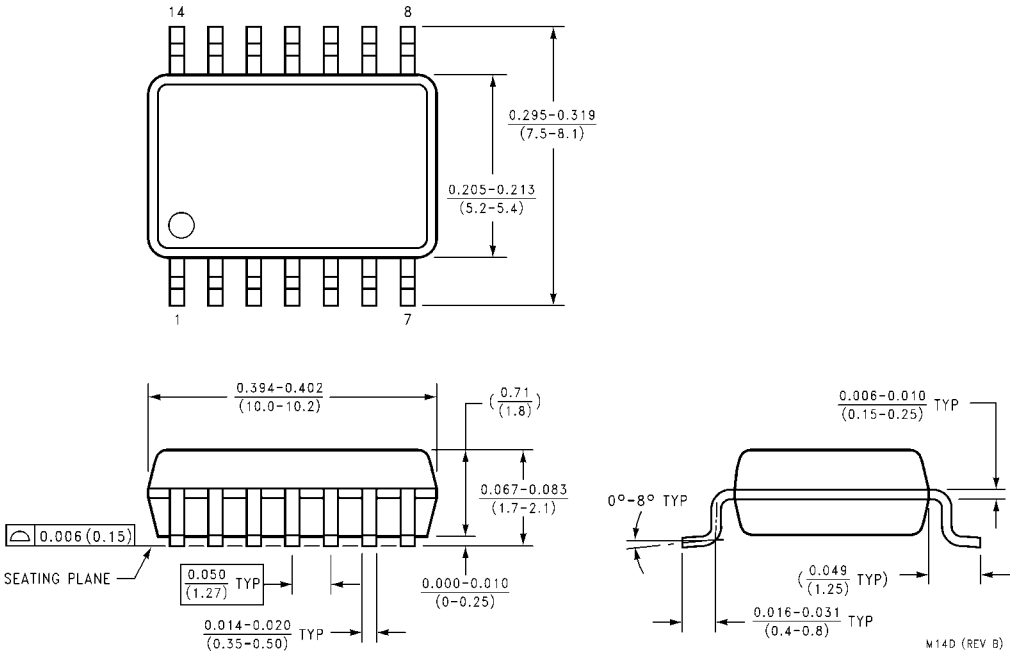
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL} t_{PLH}	Propagation Delay	3.3 ± 0.3		6.1	11.9	1.0	14.0	ns	$C_L = 15$ pF
				8.0	15.4	1.0	17.5		$C_L = 50$ pF
		5.0 ± 0.5		3.9	7.7	1.0	9.0	ns	$C_L = 15$ pF
				5.9	9.7	1.0	11.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			16				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * I_{IN} + I_{CC}/4$ (per gate)

Physical Dimensions inches (millimeters) unless otherwise noted

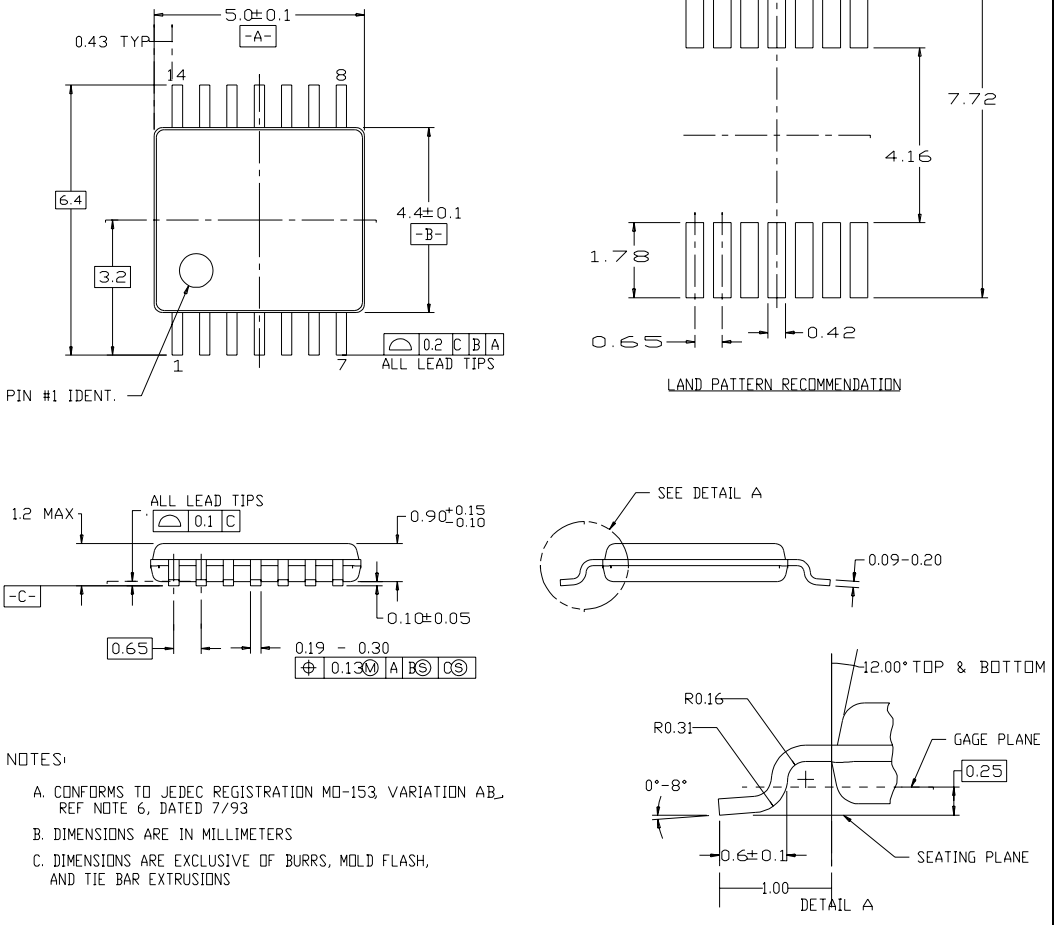


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

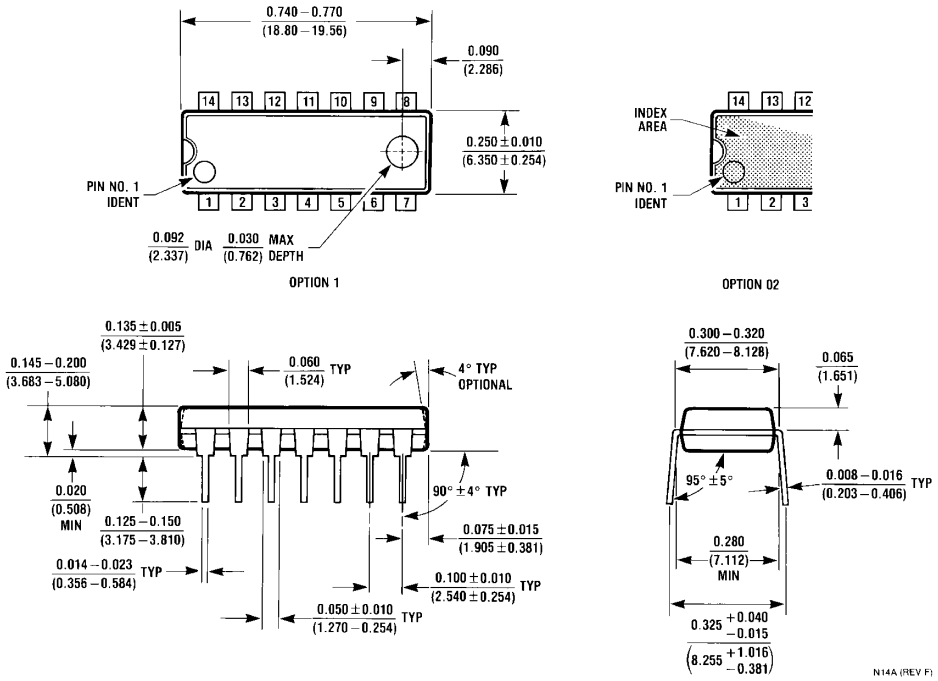
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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November 1992
Revised April 1999

74VHC138
3-to-8 Decoder/Demultiplexer

General Description

The VHC138 is an advanced high speed CMOS 3-to-8 decoder/demultiplexer fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A_0, A_1 and A_2) determine which one of the outputs ($\overline{O}_0$–$\overline{O}_7$) will go LOW. When enable input E_3 is held LOW or either $\overline{E}_1$ or $\overline{E}_2$ is held HIGH, decoding function is inhibited and all outputs go HIGH. E_3, $\overline{E}_1$ and $\overline{E}_2$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

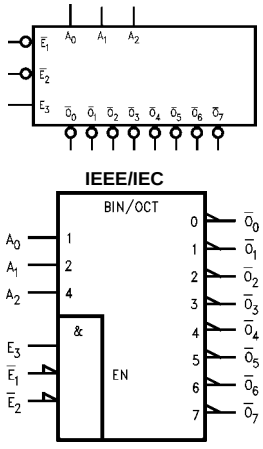
- High Speed: t_{PD} = 5.7ns (typ) at T_A = 25°C
- Low power dissipation: I_{CC} = 4 μA (max.) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min.)
- Power down protection provided on all inputs
- Pin and function compatible with 74HC138

Ordering Code:

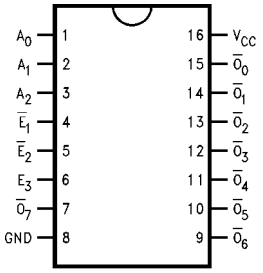
Order Number	Package Number	Package Description
74VHC138M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC138MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC138N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_2	Address Inputs
$\overline{E}_1$–$\overline{E}_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Table

Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

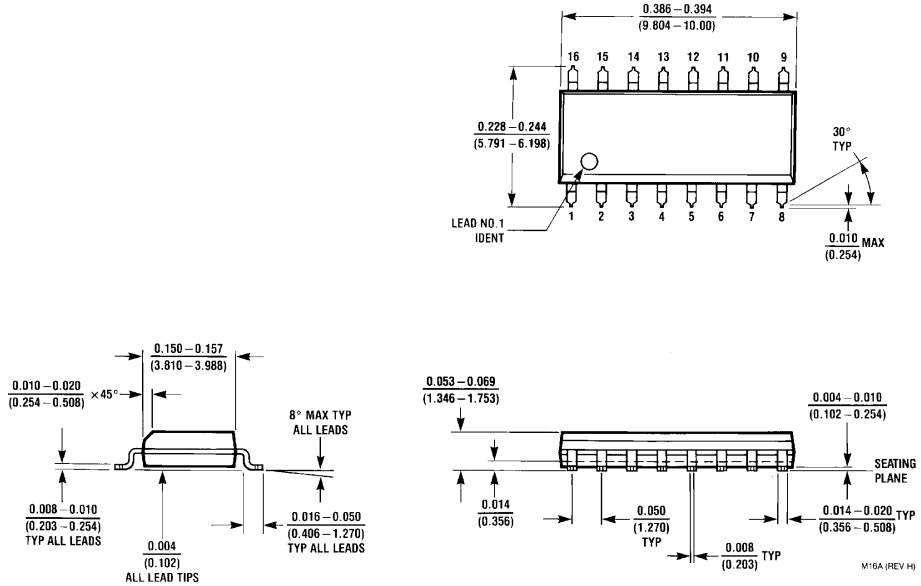
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

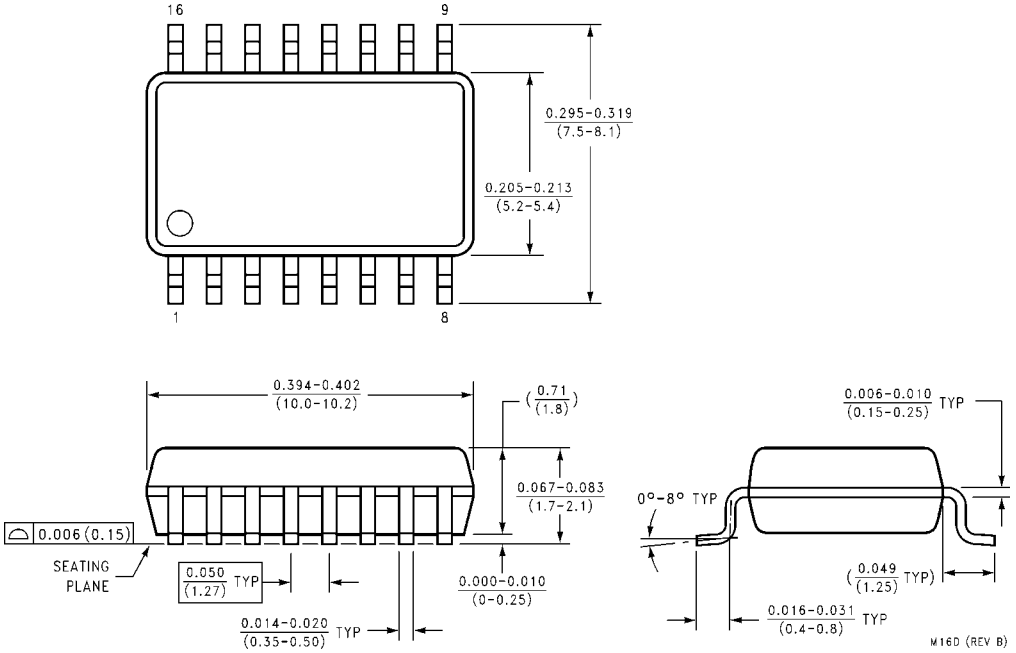
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.2	11.4	1.0	13.5	ns	$C_L = 15$ pF
t_{PHL}	A_n to $\overline{O}_n$			10.0	15.8	1.0	18.0		$C_L = 50$ pF
		5.0 ± 0.5		5.7	8.1	1.0	9.5	ns	$C_L = 15$ pF
				7.2	10.1	1.0	11.5		$C_L = 50$ pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.1	12.8	1.0	15.0	ns	$C_L = 15$ pF
t_{PHL}	E_3 to $\overline{O}_n$			10.6	16.3	1.0	18.5		$C_L = 50$ pF
		5.0 ± 0.5		5.6	8.1	1.0	9.5	ns	$C_L = 15$ pF
				7.1	10.1	1.0	11.5		$C_L = 50$ pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.2	11.4	1.0	13.5	ns	$C_L = 15$ pF
t_{PHL}	$\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$			10.7	14.9	1.0	17.0		$C_L = 50$ pF
		5.0 ± 0.5		5.8	8.1	1.0	9.5	ns	$C_L = 15$ pF
				7.3	10.1	1.0	11.5		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			34				pF	(Note 3)

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}$.

Physical Dimensions inches (millimeters) unless otherwise noted

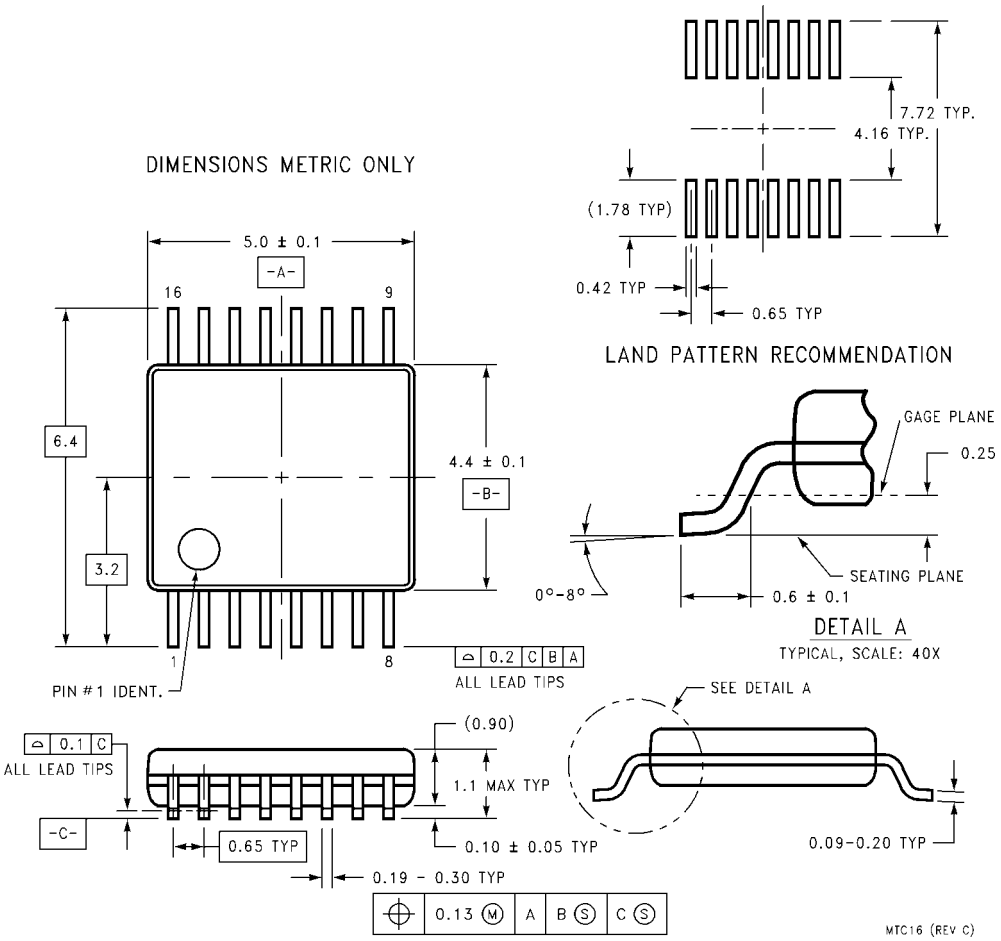


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



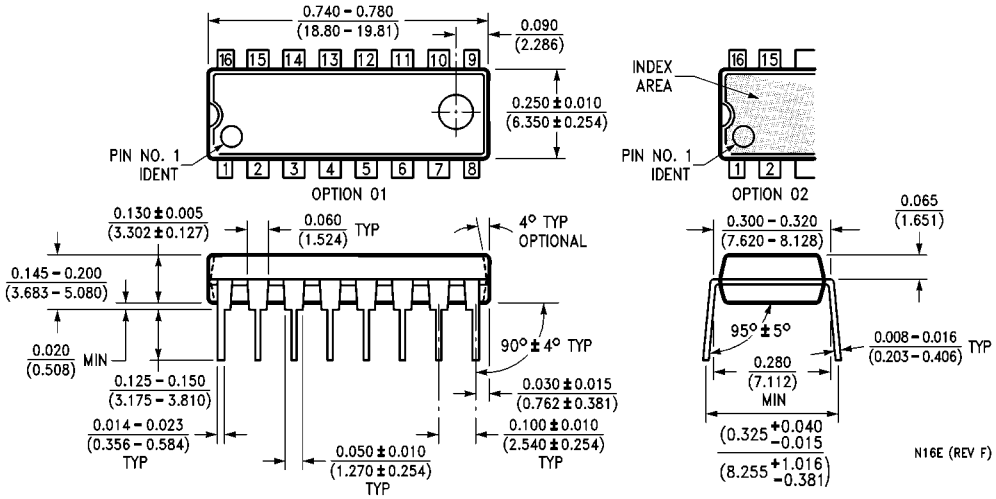
16-Lead Small Outline Package (SOP) EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1992
Revised April 1999

74VHC139
Dual 2-to-4 Decoder/Demultiplexer

General Description

The VHC139 is an advanced high speed CMOS Dual 2-to-4 Decoder/Demultiplexer fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The active LOW enable input can be used for gating or it can be used as a data input for demultiplexing applications. When the enable input is held HIGH, all four outputs are fixed at a HIGH logic level independent of the other inputs. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

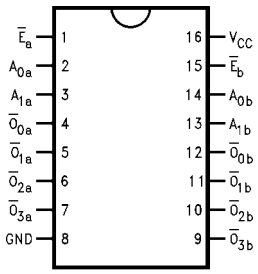
- High Speed: t_{PD} = 5.0 ns (typ) at T_A = 25°C
- Low power dissipation: I_{CC} = 4 μA (Max.) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC139

Ordering Code:

Order Number	Package Number	Package Description
74VHC139M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC139SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC139MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC139N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Description

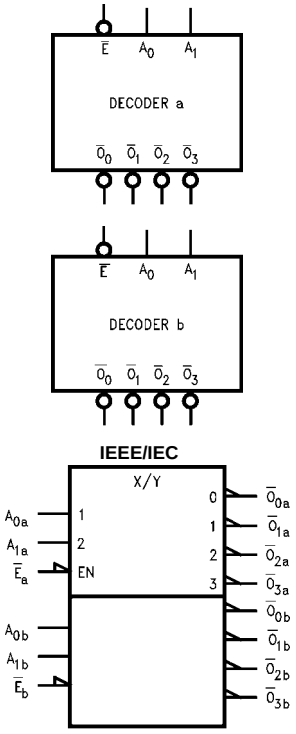
Pin Names	Description
A_0, A_1	Address Inputs
$\overline{E}$	Enable Inputs
$\overline{O}_0$–$\overline{O}_3$	Outputs

Truth Table

Inputs			Outputs			
$\overline{E}$	A_0	A_1	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	H	L	H	L	H	H
L	L	H	H	H	L	H
L	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Symbols



Functional Description

The VHC139 is a high-speed dual 2-to-4 decoder/demultiplexer. The device has two independent decoders, each of which accepts two binary weighted inputs (A_0–A_1) and provides four mutually exclusive active-LOW outputs ($\overline{O}_0$–$\overline{O}_3$). Each decoder has an active-LOW enable ($\overline{E}$). When $\overline{E}$ is HIGH all outputs are forced HIGH. The enable can be used as the data input for a 4-output demultiplexer application. Each half of the VHC139 generates all four minterms of two variables. These four minterms are useful in some applications, replacing multiple gate functions as shown in *Figure 1*, and thereby reducing the number of packages required in a logic network.

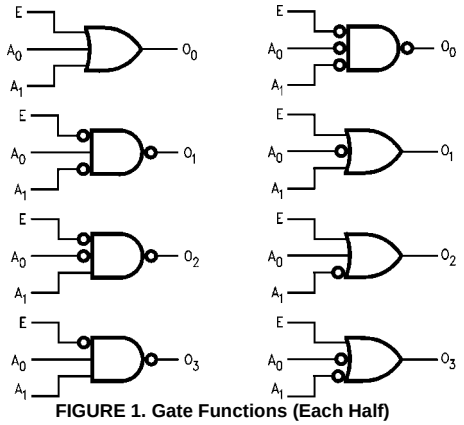
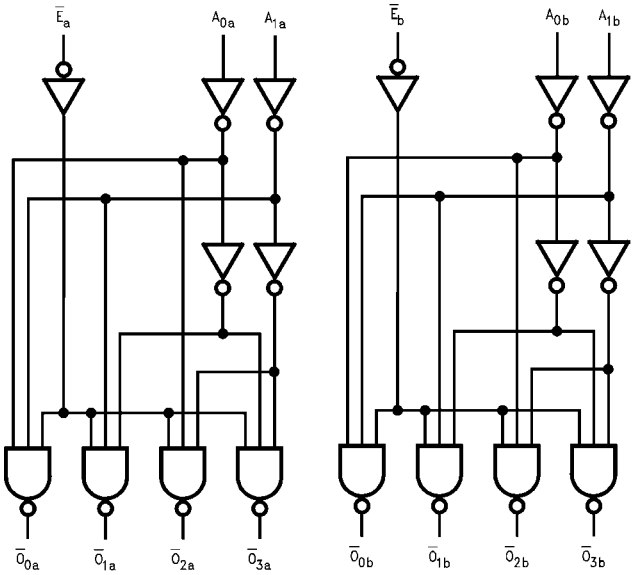


FIGURE 1. Gate Functions (Each Half)

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

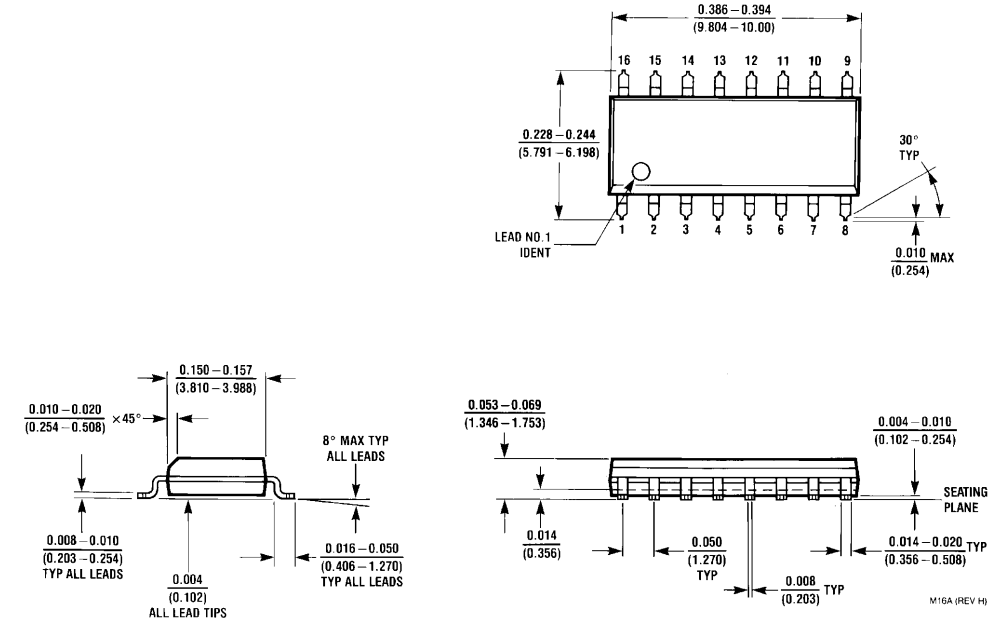
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.50		0.50	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
	Output Voltage	3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

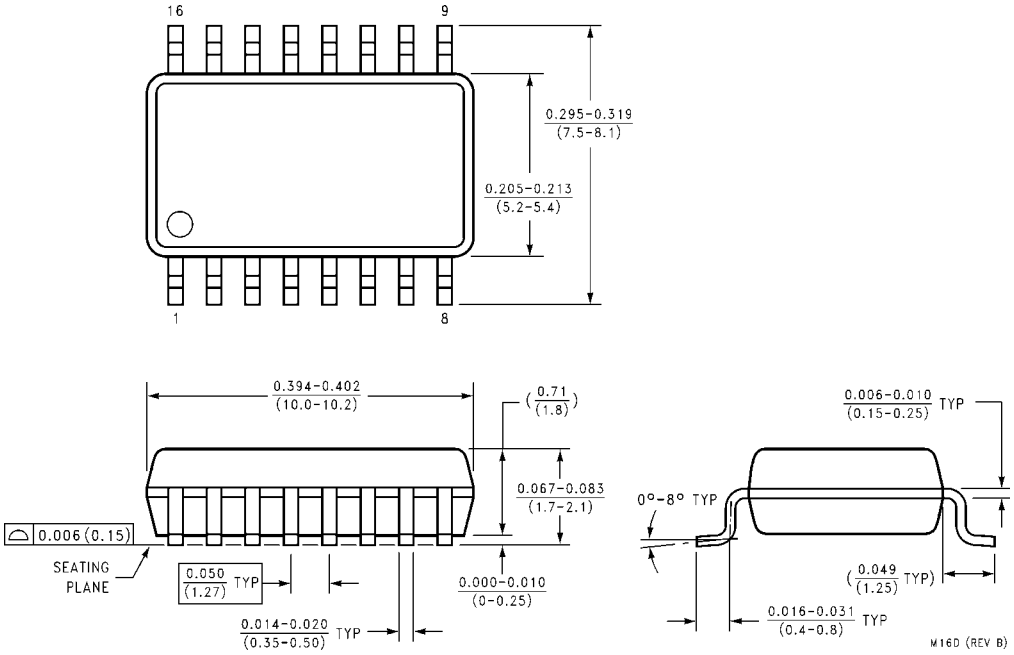
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	3.3 ± 0.3		7.2	11.0	1.0	13.0	ns	C_L = 15 pF
t_{PHL}	A_n to $\overline{O}_n$			9.7	14.5	1.0	16.5		C_L = 50 pF
		5.0 ± 0.5		5.0	7.2	1.0	8.5	ns	C_L = 15 pF
				6.5	9.2	1.0	10.5		C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		6.4	9.2	1.0	11.0	ns	C_L = 15 pF
t_{PHL}	$\overline{E}_n$ to $\overline{O}_n$			8.9	12.7	1.0	14.5		C_L = 50 pF
		5.0 ± 0.5		4.4	6.3	1.0	7.5	ns	C_L = 15 pF
				5.9	8.3	1.0	9.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			26				pF	(Note 3)

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/2 (per decoder).

Physical Dimensions inches (millimeters) unless otherwise noted

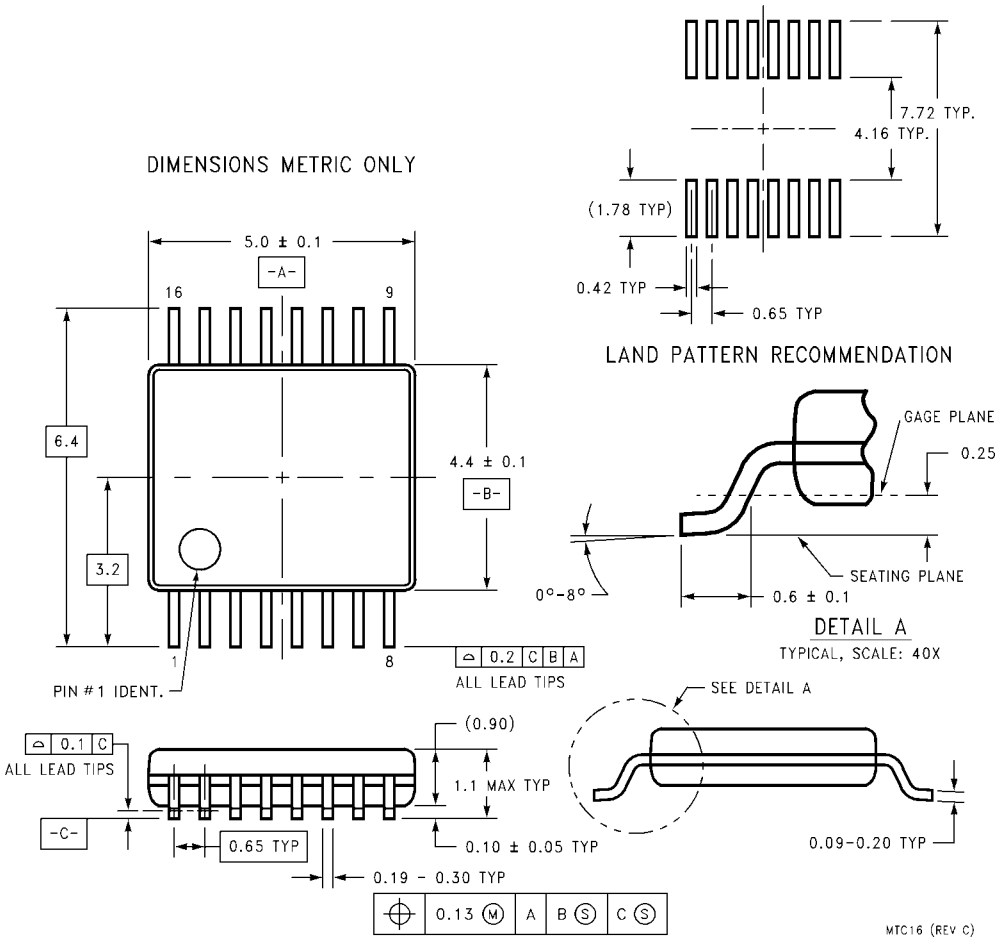


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



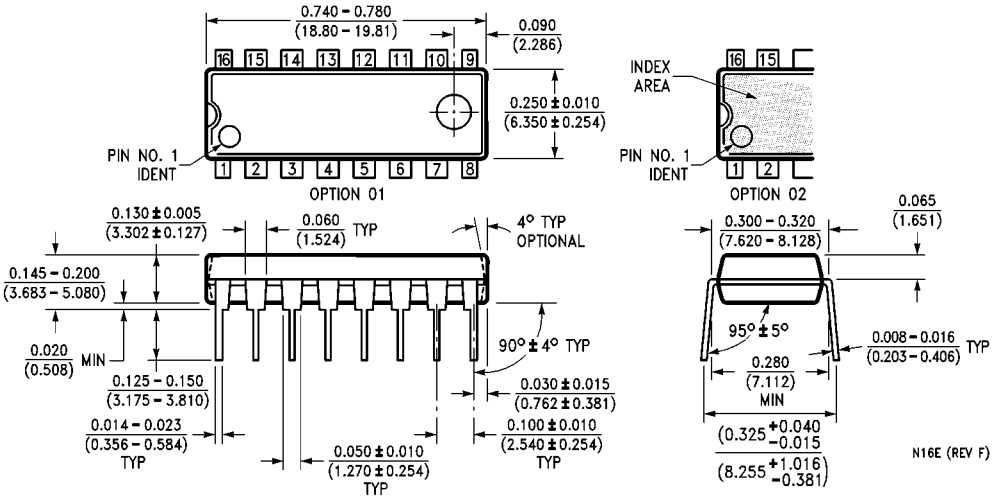
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

June 1993
Revised April 1999

74VHC14
Hex Schmitt Inverter

General Description

The VHC14 is an advanced high speed CMOS Hex Schmitt Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the VHC04 but the inputs have hysteresis between the positive-going and negative-going input thresholds, which are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals, thus providing greater noise margin than conventional inverters.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

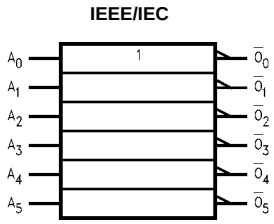
- High Speed: t_{PD} = 5.5 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 2 μA (Max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (Max)
- Pin and function compatible with 74HC14

Ordering Code:

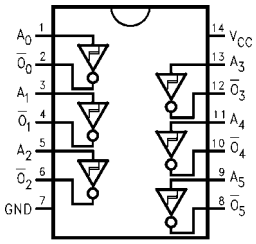
Order Number	Package Number	Package Description
74VHC14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHC14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC14N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	O
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
Soldering (10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	+2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The data book specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_P	Positive Threshold Voltage	3.0			2.20		2.20	V		
		4.5			3.15		3.15			
		5.5			3.85		3.85			
V_N	Negative Threshold Voltage	3.0	0.90			0.90		V		
		4.5	1.35			1.35				
		5.5	1.65			1.65				
V_H	Hysteresis Voltage	3.0	0.30		1.20	0.30	1.20	V		
		4.5	0.40		1.40	0.40	1.40			
		5.5	0.50		1.60	0.50	1.60			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC}	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

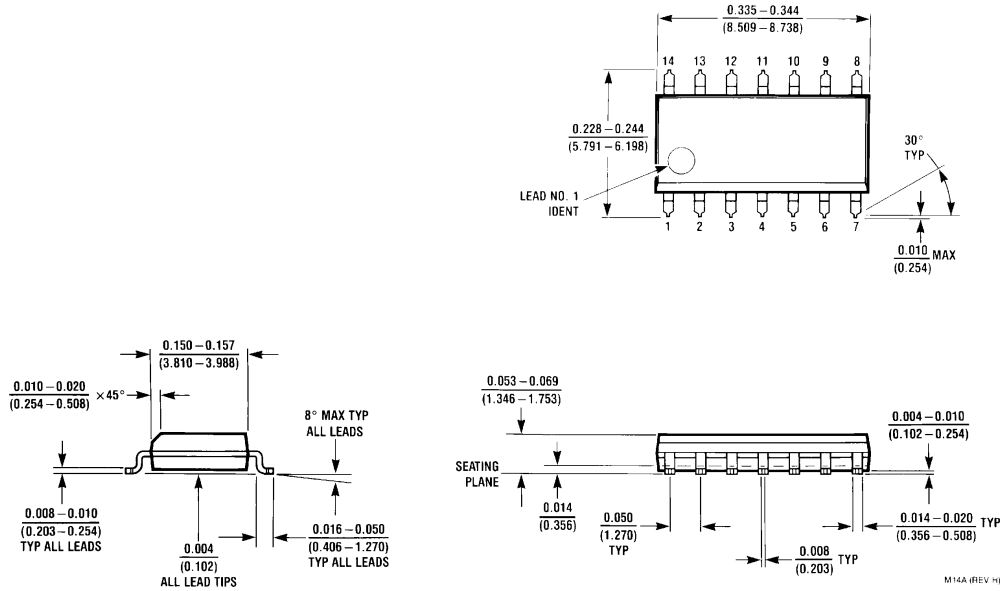
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

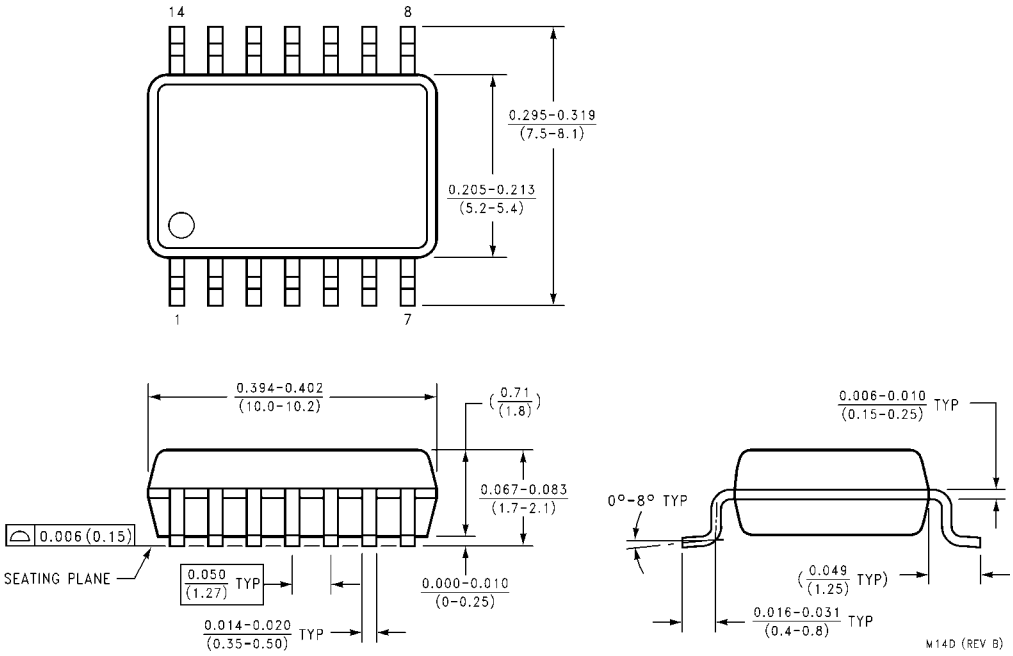
Symbol	Parameter	V_{CC}	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	$C_L = 15$ pF
t_{PHL}	Time			10.8	16.3	1.0	18.5		$C_L = 50$ pF
		5.0 ± 0.5		5.5	8.6	1.0	10.0	ns	$C_L = 15$ pF
				7.0	10.6	1.0	12.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			21				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (Opr) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/6 (per Gate)

Physical Dimensions inches (millimeters) unless otherwise noted

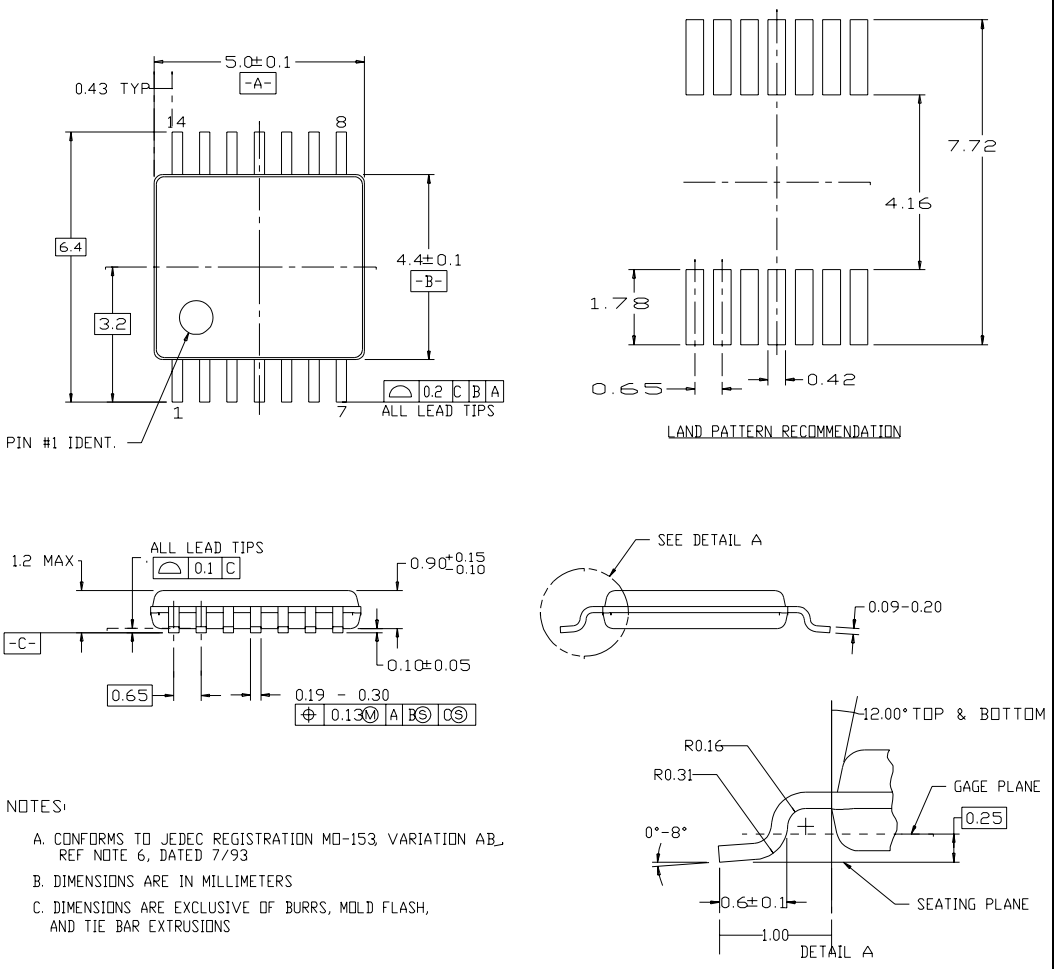


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

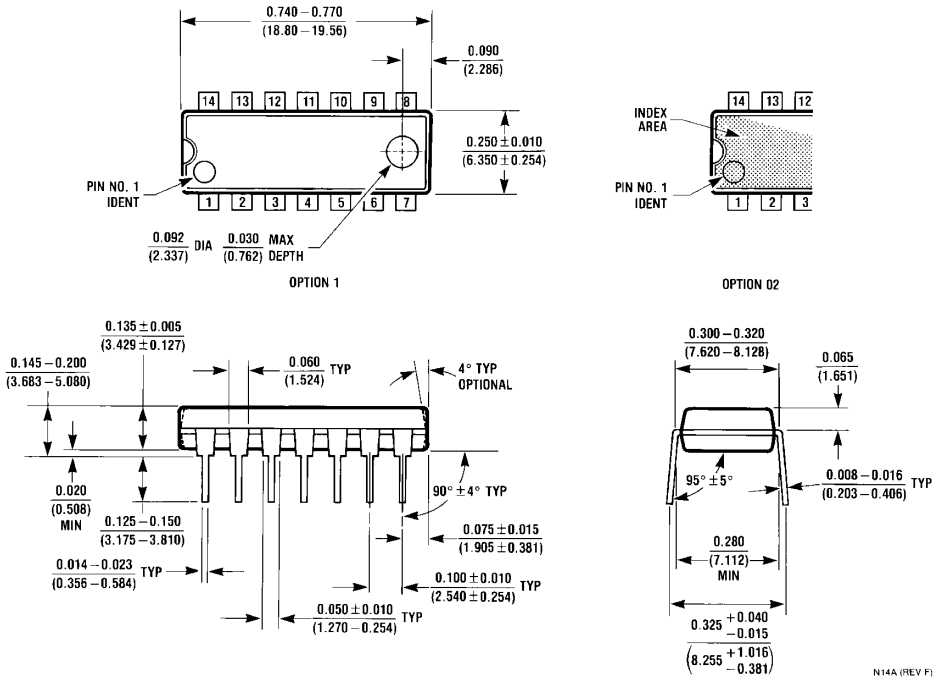
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised April 1999

74VHC153
Dual 4-Input Multiplexer

General Description

The VHC153 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC153 is a high-speed Dual 4-Input Multiplexer with common select inputs and individual enable inputs for each section. It can select two lines of data from four sources. The two buffered outputs present data in the true (non-inverted) form. In addition to multiplexer operation, the VHC153 can act as a function generator and generate any two functions of three variables. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

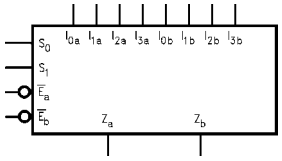
- High Speed: t_{PD} = 5.0 ns at T_A = 25°C
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC153

Ordering Code:

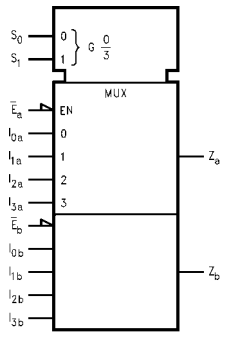
Order Number	Package Number	Package Description
74VHC153M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC153SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC153MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC153N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

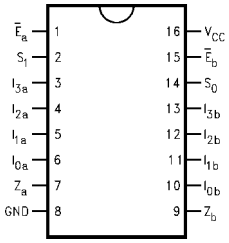
Logic Symbols



IEEC/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{3a}	Side A Data Inputs
I_{0b}–I_{3b}	Side B Data Inputs
S_0, S_1	Common Select Inputs
$\overline{E}_a$	Side A Enable Input
$\overline{E}_b$	Side B Enable Input
Z_a	Side A Output
Z_b	Side B Output

Functional Description

The VHC153 is a dual 4-input multiplexer. It can select two bits of data from up to four sources under the control of the common Select inputs (S_0, S_1). The two 4-input multiplexer circuits have individual active-LOW Enables ($\overline{E}_a$, $\overline{E}_b$) which can be used to strobe the outputs independently. When the Enables ($\overline{E}_a$, $\overline{E}_b$) are HIGH, the corresponding outputs (Z_a, Z_b) are forced LOW. The VHC153 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the Select inputs. The logic equations for the outputs are shown below.

$$Z_a = \overline{E}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet S_0 + I_{3a} \bullet S_1 \bullet S_0)$$

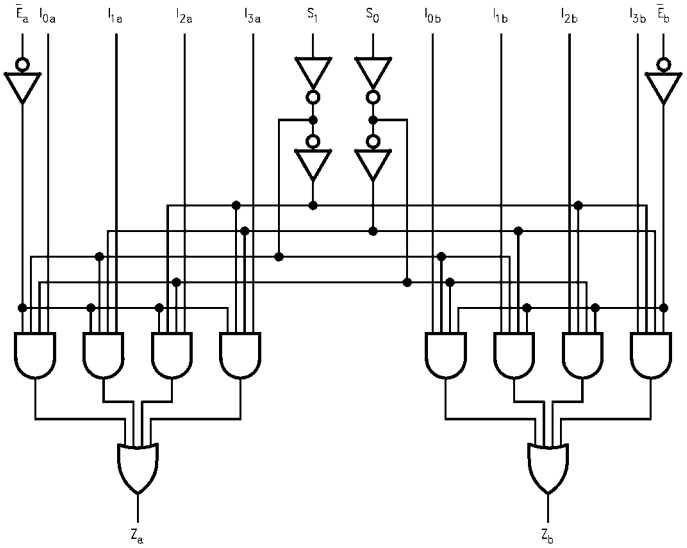
$$Z_b = \overline{E}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet S_0 + I_{3b} \bullet S_1 \bullet S_0)$$

Truth Table

Select Inputs		Inputs (a or b)					Output
S_0	S_1	$\overline{E}$	I_0	I_1	I_2	I_3	Z
X	X	H	X	X	X	X	L
L	L	L	L	X	X	X	L
L	L	L	H	X	X	X	H
H	L	L	X	L	X	X	L
H	L	L	X	H	X	X	H
L	H	L	X	X	L	X	L
L	H	L	X	X	H	X	H
H	H	L	X	X	X	L	L
H	H	L	X	X	X	H	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to + 7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 5.5V
Input Voltage (V_{IN})	0V to +5.5
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0~100 ns/V
V_{CC} = 5.0V ± 0.5V	0~20 ns/V

Note 1: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

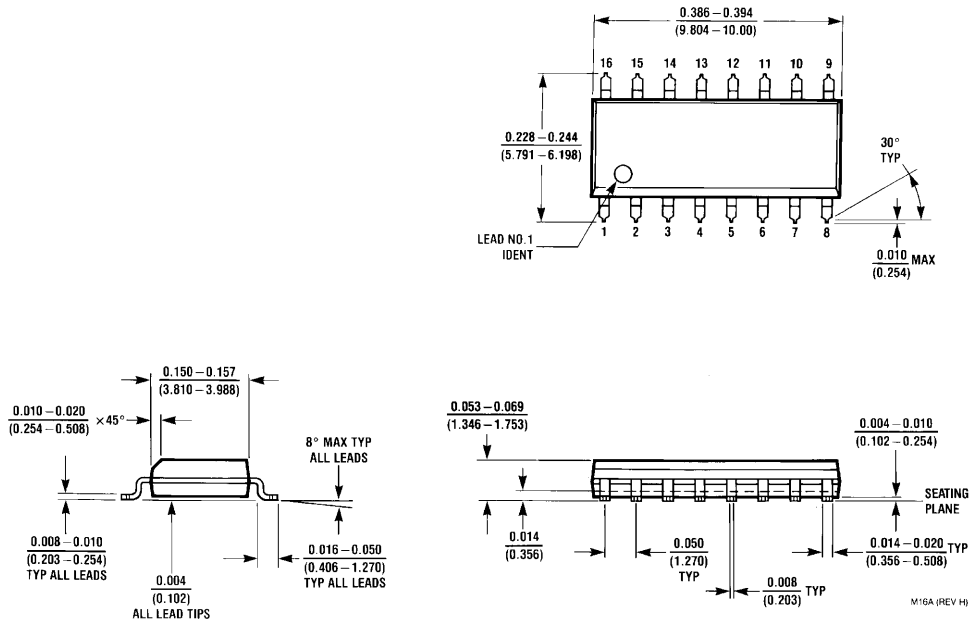
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

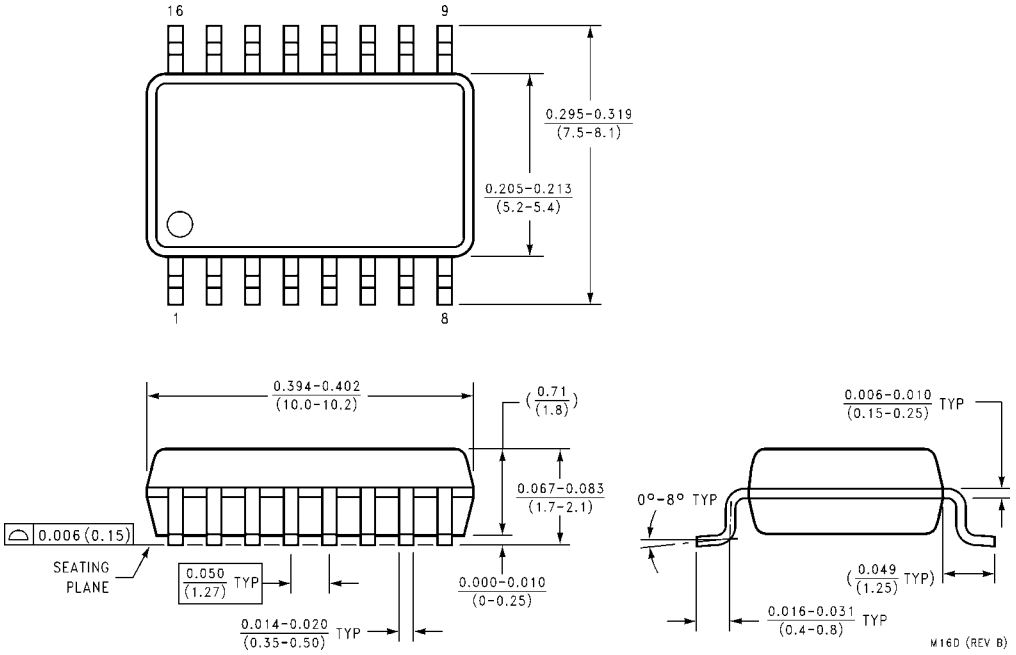
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	3.3 ± 0.3		7.7	11.9	1.0	14.0	ns	C_L = 15 pF
t_{PHL}	I_n to Z_n			10.2	15.4	1.0	17.5		C_L = 50 pF
		5.0 ± 0.5		5.0	7.7	1.0	9.0	ns	C_L = 15 pF
				6.5	9.7	1.0	11.0		C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		10.8	16.7	1.0	19.5	ns	C_L = 15 pF
t_{PHL}	S_n to Z_n			13.3	20.2	1.0	23.0		C_L = 50 pF
		5.0 ± 0.5		6.8	9.9	1.0	11.5	ns	C_L = 15 pF
				8.3	11.9	1.0	13.5		C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		6.3	10.1	1.0	12.0	ns	C_L = 15 pF
t_{PHL}	$\overline{E}_n$ to Z_n			8.8	13.6	1.0	15.5		C_L = 50 pF
		5.0 ± 0.5		4.4	6.4	1.0	7.5	ns	C_L = 15 pF
				5.9	8.4	1.0	9.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			20				pF	(Note 3)

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

Physical Dimensions inches (millimeters) unless otherwise noted

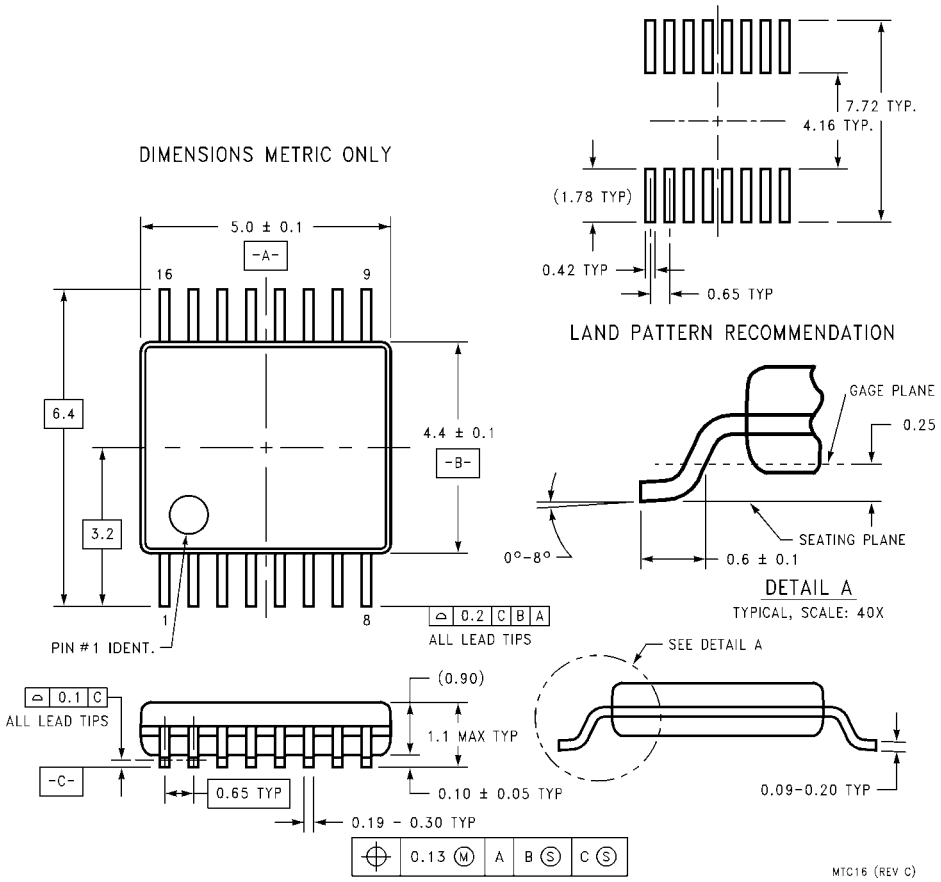


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



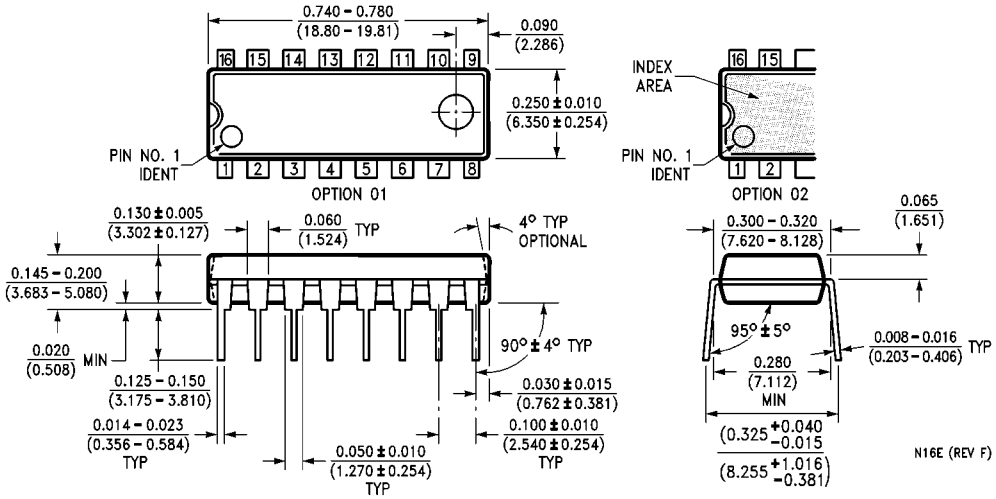
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

November 1992
Revised April 1999

74VHC157
Quad 2-Input Multiplexer

General Description

The VHC157 is an advanced high speed CMOS Quad 2-Channel Multiplexer fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of four 2-input digital multiplexers with common select and enable inputs. When the $\overline{\text{ENABLE}}$ input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the I_{0x} or I_{1x} inputs get routed to their corresponding outputs.

An Input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

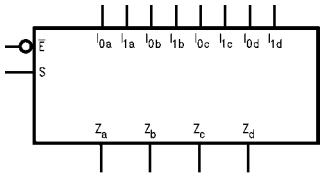
- High Speed: t_{PD} = 4.1 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max.) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min.)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max.)
- Pin and function compatible with 74HC157

Ordering Code:

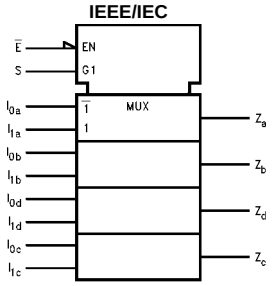
Order Number	Package Number	Package Description
74VHC157M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC157SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC157MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC157N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

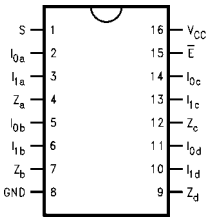
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{E}$	Enable Input
S	Select Input
Z_a–Z_d	Outputs

Truth Table

Inputs				Outputs
$\overline{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

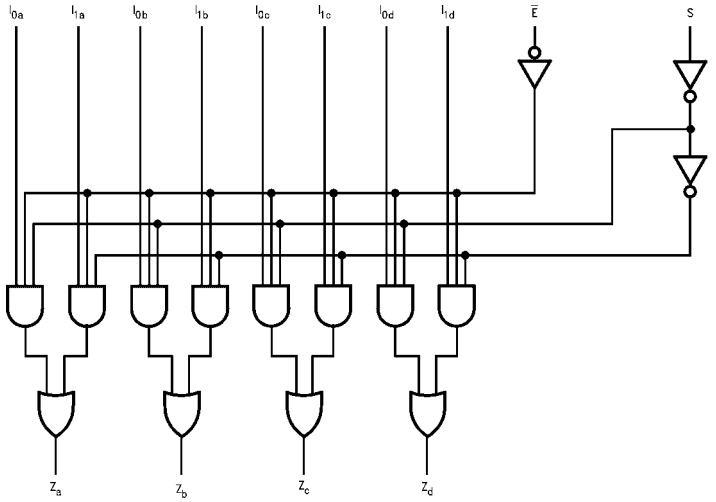
Functional Description

The VHC157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\overline{E}$) is active-LOW. When $\overline{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The VHC157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$$Z_a = \overline{E} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$$
$$Z_b = \overline{E} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$$
$$Z_c = \overline{E} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$$
$$Z_d = \overline{E} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$$

A common use of the VHC157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The VHC157 can generate any four of the sixteen different functions of two variables with one variable common. This is useful for implementing gating functions.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

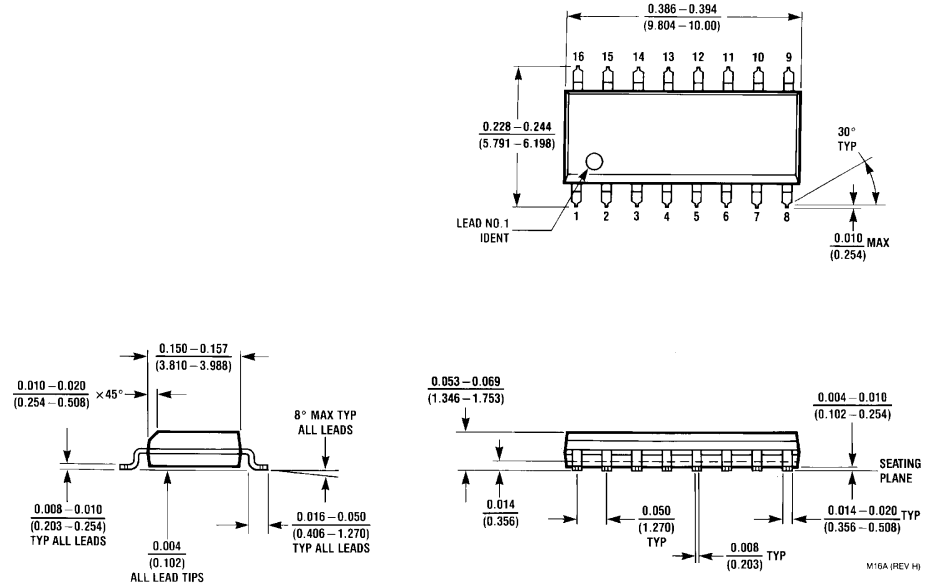
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

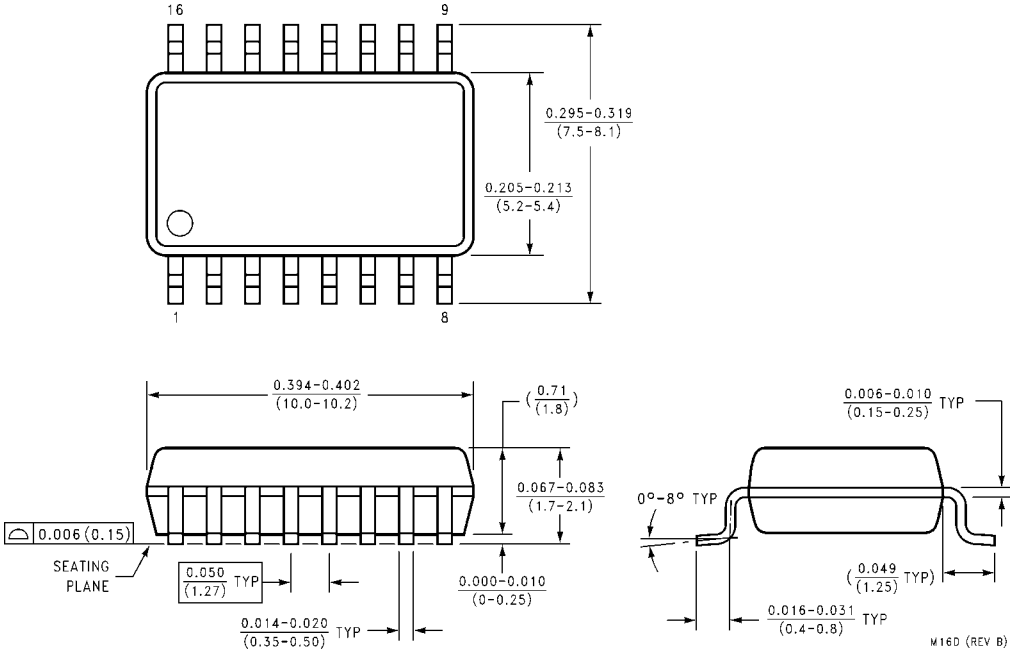
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	3.3 ± 0.3		6.2	9.7	1.0	11.5	ns	C_L = 15 pF
t_{PHL}	I_n to Z_n			8.7	13.2	1.0	15.0		C_L = 50 pF
		5.0 ± 0.5		4.1	6.4	1.0	7.5	ns	C_L = 15 pF
				5.6	8.4	1.0	9.5		C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.4	13.2	1.0	15.5	ns	C_L = 15 pF
t_{PHL}	S to Z_n			10.9	16.7	1.0	19.0		C_L = 50 pF
		5.0 ± 0.5		5.3	8.1	1.0	9.5	ns	C_L = 15 pF
				6.8	10.1	1.0	11.5		C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.7	13.6	1.0	16.0	ns	C_L = 15 pF
t_{PHL}	$\overline{E}$ to Z_n			11.2	17.1	1.0	19.5		C_L = 50 pF
		5.0 ± 0.5		5.6	8.6	1.0	10.0	ns	C_L = 15 pF
				7.1	10.6	1.0	12.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			20				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

Physical Dimensions inches (millimeters) unless otherwise noted

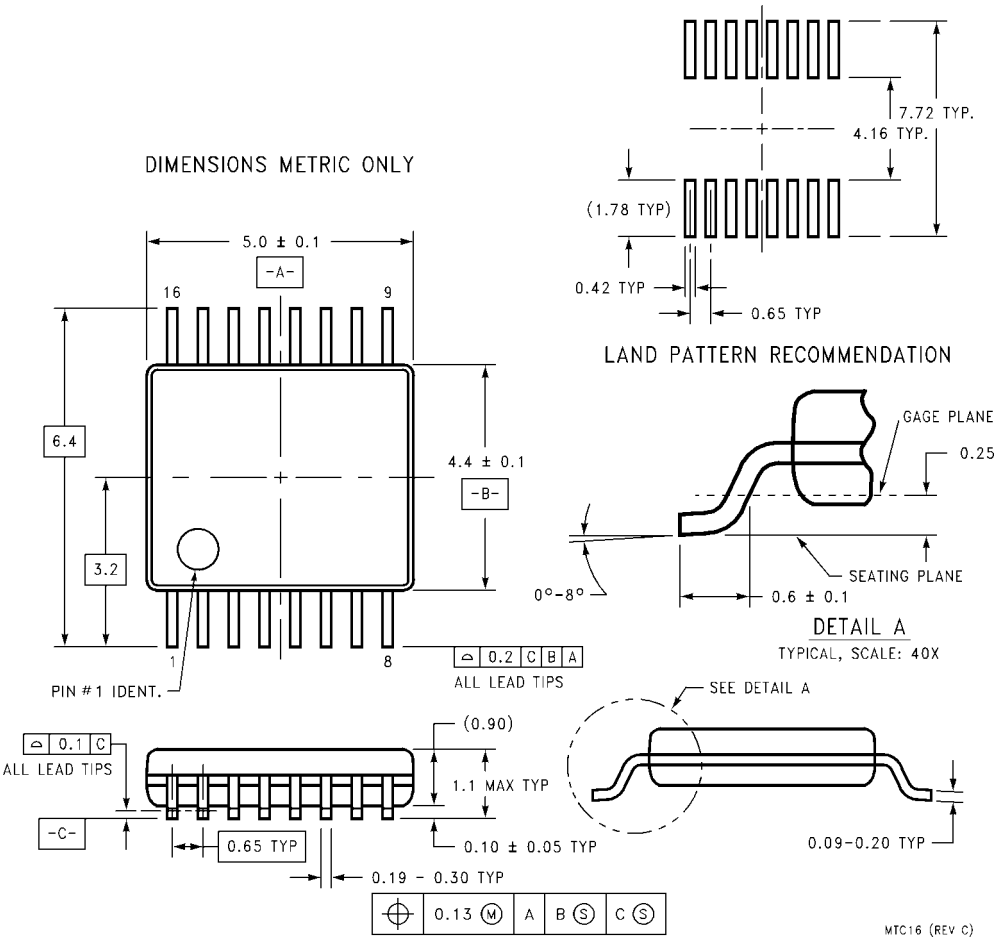


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



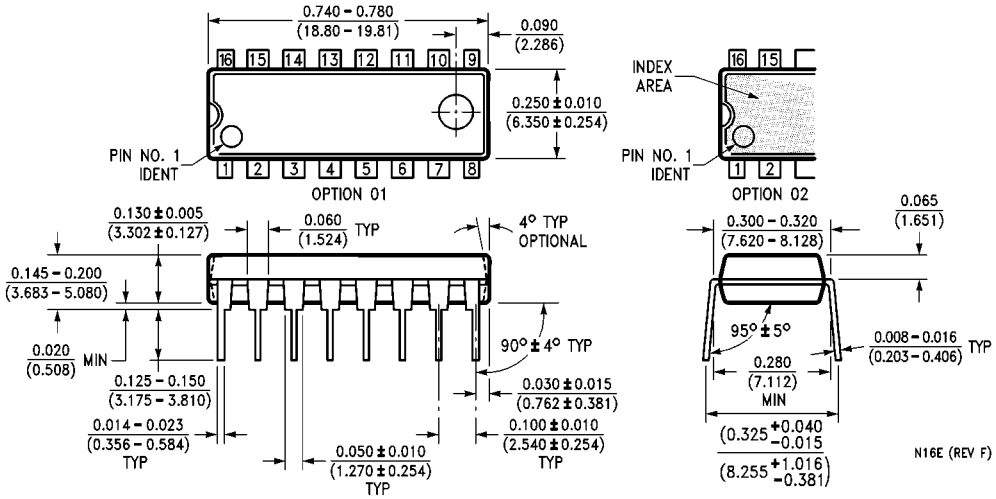
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised April 1999

74VHC161
4-Bit Binary Counter with Asynchronous Clear

General Description

The VHC161 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC161 is a high-speed synchronous modulo-16 binary counter. This device is synchronously presettable for application in programmable dividers and have two types of Count Enable inputs plus a Terminal Count output for versatility in forming synchronous multistage counters. The VHC161 has an asynchronous Master Reset input that overrides all other inputs and forces the outputs LOW. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

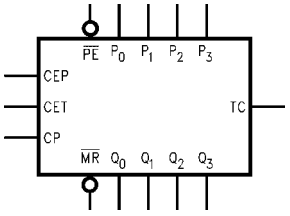
- High Speed:
  f_{MAX} = 185 MHz (typ) at T_A = 25°C
- Synchronous counting and loading
- High-speed synchronous expansion
- Low power dissipation:
  I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC161

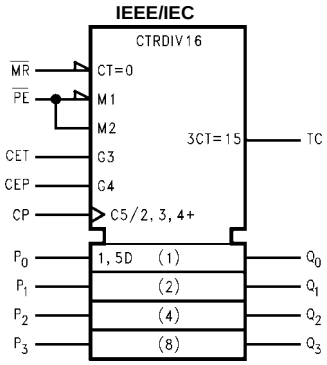
Ordering Code:

Order Number	Package Number	Package Description
74VHC161M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC161SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC161MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC161N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

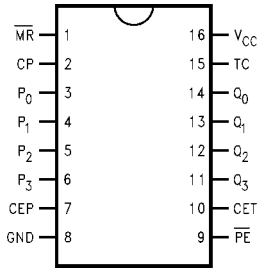
Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
CEP	Count Enable Parallel Input
CET	Count Enable Trickle Input
CP	Clock Pulse Input
$\overline{MR}$	Asynchronous Master Reset Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Inputs
Q_0–Q_3	Flip-Flop Outputs
TC	Terminal Count Output

Functional Description

The VHC161 counts in modulo-16 binary sequence. From state 15 (HHHH) it increments to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs (except due to Master Reset of the VHC161) occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: asynchronous reset, parallel load, count-up and hold. Five control inputs—Master Reset, Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides all other inputs and asynchronously forces all outputs LOW. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{MR}$ HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The VHC161 uses D-type edge-triggered flip-flops and changing the $\overline{PE}$, CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 15. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to TC delay of the first stage, plus the cumulative CET to TC delays of the intermediate stages, plus the CET to CP setup time of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in *Figure 2* are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle requires 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to TC delay of the first stage plus the CEP to CP setup time of the last stage. The TC output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters.

Logic Equations: Count Enable = CEP • CET • $\overline{PE}$

$TC = Q_0 \cdot Q_1 \cdot Q_2 \cdot Q_3 \cdot CET$

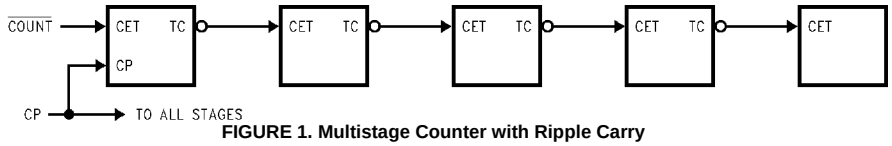


FIGURE 1. Multistage Counter with Ripple Carry

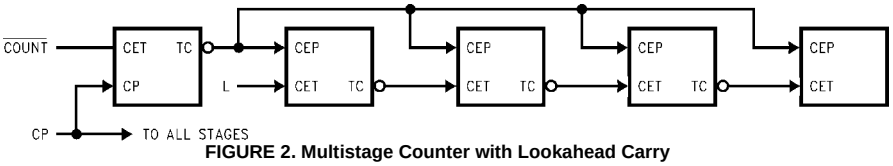


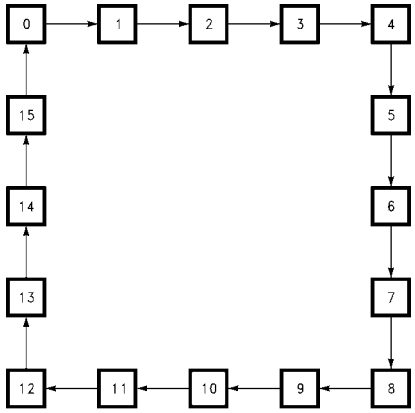
FIGURE 2. Multistage Counter with Lookahead Carry

Mode Select Table

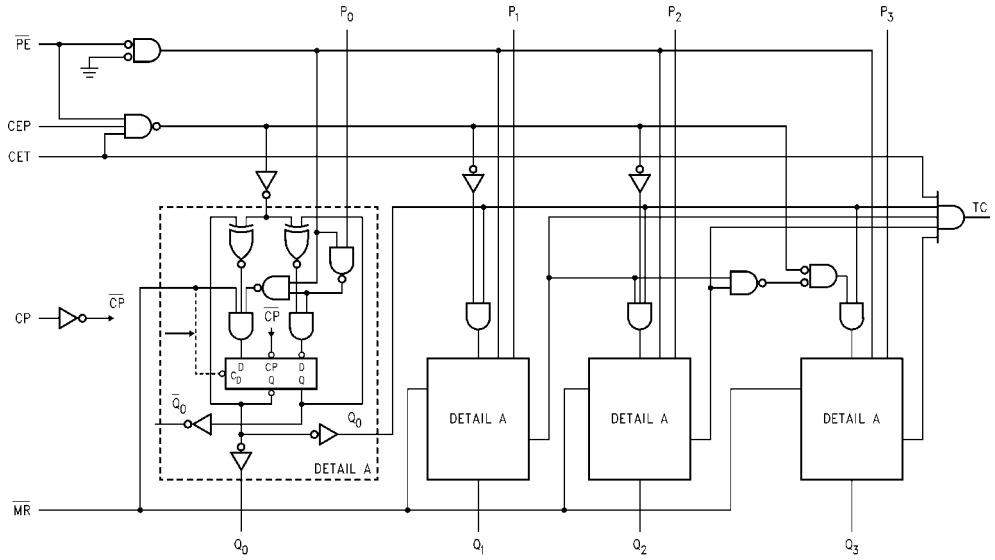
$\overline{MR}$	$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (⌐)
L	X	X	X	Reset (Clear)
H	L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	H	Count (Increment)
H	H	L	X	No Change (Hold)
H	H	X	L	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagram



Block Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Time (CP–Q_n)	3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	C_L = 15 pF
				10.8	16.3	1.0	18.5		C_L = 50 pF
		5.0 ± 0.5		4.9	8.1	1.0	9.5	ns	C_L = 15 pF
				6.4	10.1	1.0	11.5		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP–TC, Count)	3.3 ± 0.3		8.7	13.6	1.0	16.0	ns	C_L = 15 pF
				11.2	17.1	1.0	19.5		C_L = 50 pF
		5.0 ± 0.5		4.9	8.1	1.0	9.5	ns	C_L = 15 pF
				6.4	10.1	1.0	11.5		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP–TC, Load)	3.3 ± 0.3		11.0	17.2	1.0	20.0	ns	C_L = 15 pF
				13.5	20.7	1.0	23.5		C_L = 50 pF
		5.0 ± 0.5		6.2	10.3	1.0	12.0	ns	C_L = 15 pF
				7.7	12.3	1.0	14.0		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CET–TC)	3.3 ± 0.3		7.5	12.3	1.0	14.5	ns	C_L = 15 pF
				10.5	15.8	1.0	18.0		C_L = 50 pF
		5.0 ± 0.5		4.9	8.1	1.0	9.5	ns	C_L = 15 pF
				6.4	10.1	1.0	11.5		C_L = 50 pF
t_{PHL}	Propagation Delay Time ($\overline{MR}$ –Q_n)	3.3 ± 0.3		8.9	13.6	1.0	16.0	ns	C_L = 15 pF
				11.2	17.1	1.0	19.5		C_L = 50 pF
		5.0 ± 0.5		5.5	9.0	1.0	10.5	ns	C_L = 15 pF
				7.0	11.0	1.0	12.5		C_L = 50 pF
t_{PHL}	Propagation Delay Time ($\overline{MR}$ –TC)	3.3 ± 0.3		8.4	13.2	1.0	15.5	ns	C_L = 15 pF
				10.9	16.7	1.0	19.0		C_L = 50 pF
		5.0 ± 0.5		5.0	8.6	1.0	10.0	ns	C_L = 15 pF
				6.5	10.6	1.0	12.0		C_L = 50 pF
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	80	130		70		MHz	C_L = 15 pF
			55	85		50			C_L = 50 pF
		5.0 ± 0.5	135	185		115		MHz	C_L = 15 pF
			95	125		85			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			23				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

When the outputs drive a capacitive load, total current consumption is the sum of C_{PD}, and ΔI_{CC} which is obtained from the following formula:

$$\Delta I_{CC} = F_{CP} \bullet V_{CC} \left(\frac{C_{Q0}}{2} + \frac{C_{Q1}}{4} + \frac{C_{Q2}}{8} + \frac{C_{Q3}}{16} + \frac{C_{TC}}{16} \right)$$

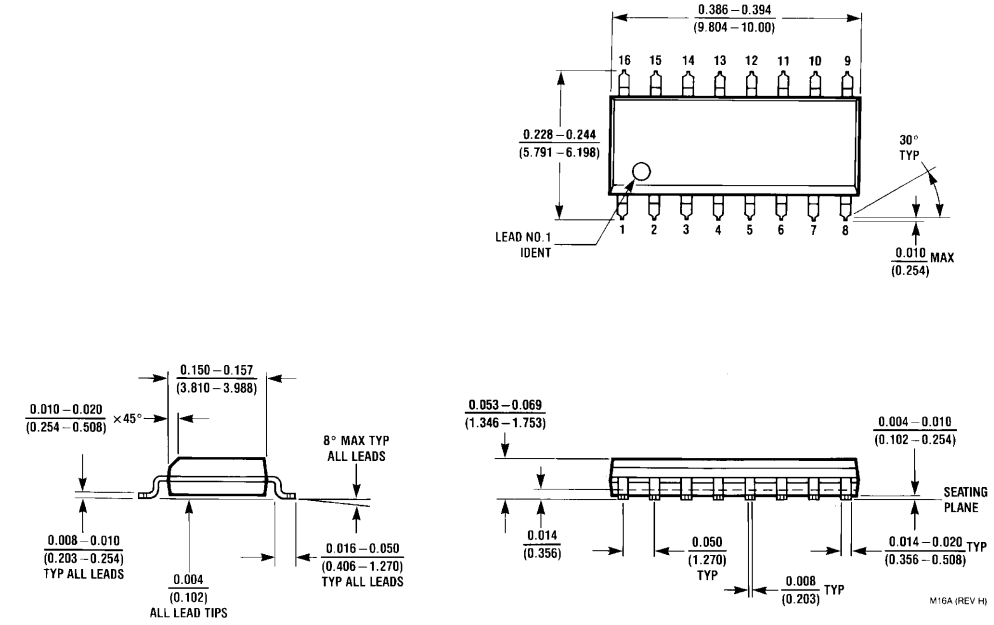
C_{Q0}–C_{Q3} and C_{TC} are the capacitances at Q0–Q3 and TC, respectively. F_{CP} is the input frequency of the CP.

AC Operating Requirements

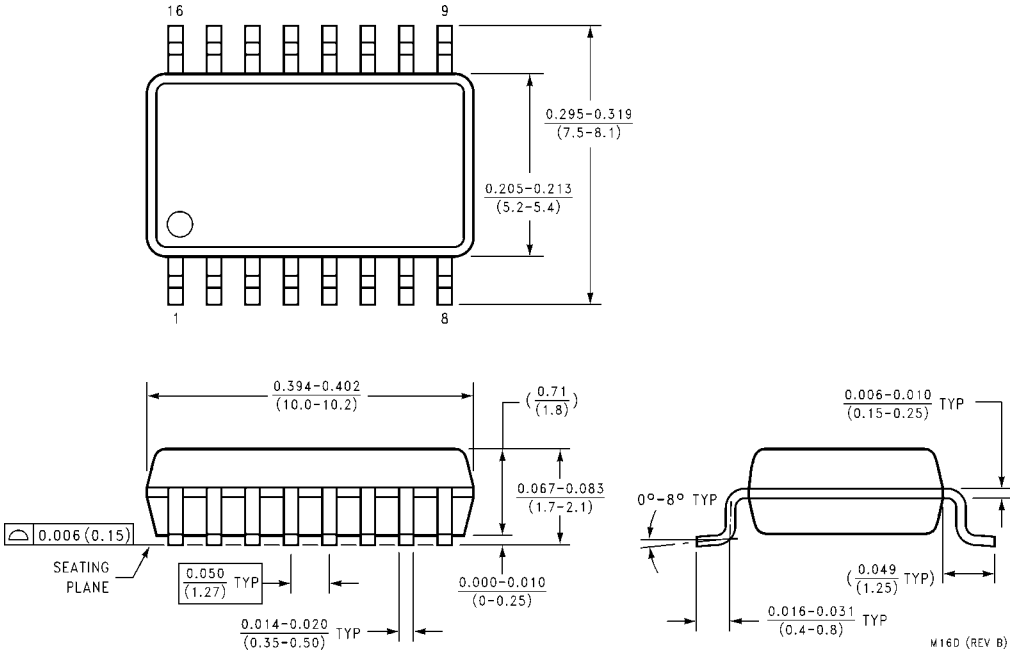
Symbol	Parameter	V_{CC} (Note 5) (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
t_S	Minimum Setup Time	3.3		5.5	6.5	ns
	(P_n–CP)	5.0		4.5	4.5	
t_S	Minimum Setup Time	3.3		8.0	9.5	ns
	($\overline{PE}$ –CP)	5.0		5.0	6.0	
t_S	Minimum Setup Time	3.3		7.5	9.0	ns
	(CEP or CET–CP)	5.0		5.0	6.0	
t_H	Minimum Hold Time	3.3		1.0	1.0	ns
	(P_n–CP)	5.0		1.0	1.0	
t_H	Minimum Hold Time	3.3		1.0	1.0	ns
	($\overline{PE}$ –CP)	5.0		1.0	1.0	
t_H	Minimum Hold Time	3.3		1.0	1.0	ns
	(CEP or CET–CP)	5.0		1.0	1.0	
$t_W(L)$	Minimum Pulse Width	3.3		5.0	5.0	ns
$t_W(H)$	CP (Count)	5.0		5.0	5.0	
$t_W(L)$	Minimum Pulse Width	3.3		5.0	5.0	ns
	($\overline{MR}$)	5.0		5.0	5.0	
t_{REC}	Minimum Removal	3.3		2.5	2.5	ns
	Time	5.0		1.5	1.5	

Note 5: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

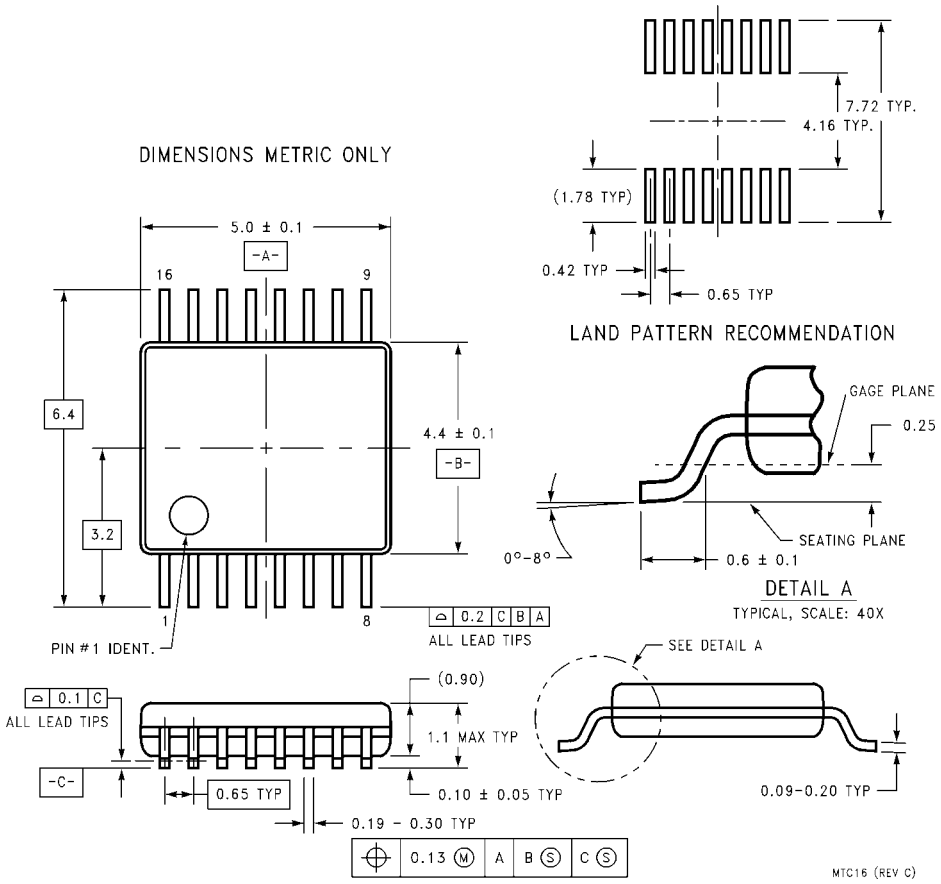


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



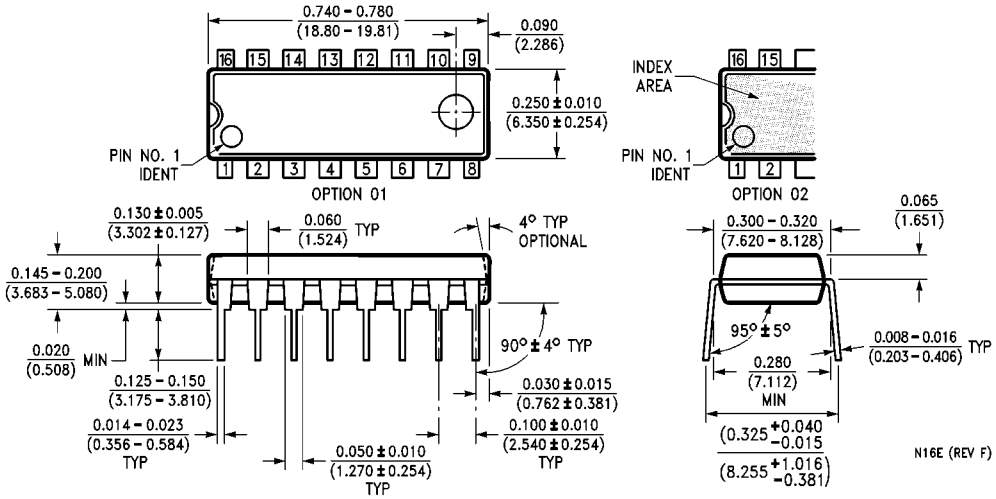
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

February 1998
Revised October 1999

74VHC161284
IEEE 1284 Transceiver

General Description

The VHC161284 contains eight bidirectional data buffers and eleven control/status buffers to implement a full IEEE 1284 compliant interface. The device supports the IEEE 1284 standard and is intended to be used in Extended Capabilities Port mode (ECP). The pinout allows for easy connection from the Peripheral (A-side) to the Host (cable side).

Outputs on the cable side can be configured to be either open drain or high drive (± 14 mA). The pull-up and pull-down series termination resistance of these outputs on the cable side is optimized to drive an external cable. In addition, all inputs (except HLH) and outputs on the cable side contain internal pull-up resistors connected to the V_{CC} supply to provide proper termination and pull-ups for open drain mode.

Outputs on the Peripheral side are standard LOW-drive CMOS outputs. The DIR input controls data flow on the A_1–A_8/B_1–B_8 transceiver pins.

Features

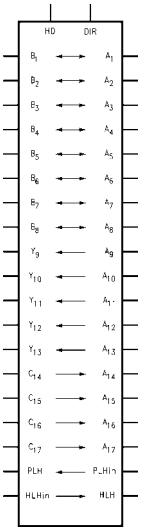
- Supports IEEE 1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals
- Replaces the function of two (2) 74ACT1284 devices
- All inputs have hysteresis to provide noise margin
- B and Y output resistance optimized to drive external cable
- B and Y outputs in high impedance mode during power down
- Inputs and outputs on cable side have internal pull-up resistors
- Flow-through pin configuration allows easy interface between the Peripheral and Host

Ordering Code:

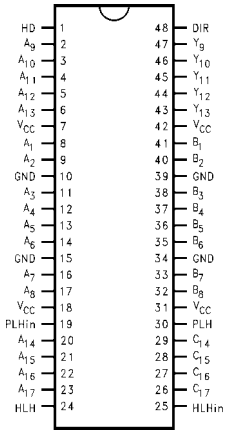
Ordering Number	Package Number	Package Description
74VHC161284MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
74VHC161284MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
HD	HIGH Drive Enable Input (Active HIGH)
DIR	Direction Control Input
A_1–A_8	Inputs or Outputs
B_1–B_8	Inputs or Outputs
A_9–A_{13}	Inputs
Y_9–Y_{13}	Outputs
A_{14}–A_{17}	Outputs
C_{14}–C_{17}	Inputs
PLH_{IN}	Peripheral Logic HIGH Input
PLH	Peripheral Logic HIGH Output
HLH_{IN}	Host Logic HIGH Input
HLH	Host Logic HIGH Output

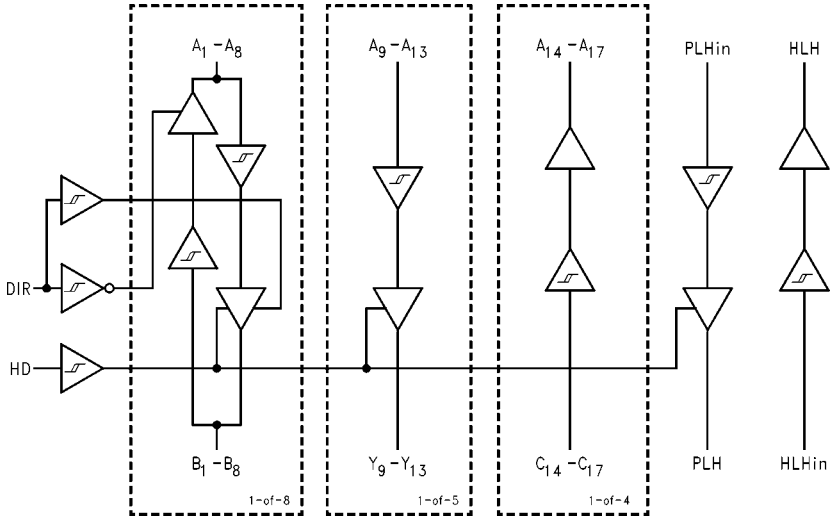
Truth Table

Inputs		Outputs
DIR	HD	
L	L	B_1–B_8 Data to A_1–A_8, and A_9–A_{13} Data to Y_9–Y_{13} (Note 1) C_{14}–C_{17} Data to A_{14}–A_{17} PLH Open Drain Mode
L	H	B_1–B_8 Data to A_1–A_8, and A_9–A_{13} Data to Y_9–Y_{13} C_{14}–C_{17} Data to A_{14}–A_{17}
H	L	A_1–A_8 Data to B_1–B_8 (Note 2) A_9–A_{13} Data to Y_9–Y_{13} (Note 1) C_{14}–C_{17} Data to A_{14}–A_{17} PLH Open Drain Mode
H	H	A_1–A_8 Data to B_1–B_8 A_9–A_{13} Data to Y_9–Y_{13} C_{14}–C_{17} Data to A_{14}–A_{17}

Note 1: Y_9–Y_{13} Open Drain Outputs

Note 2: B_1–B_8 Open Drain Outputs

Logic Diagram



Absolute Maximum Ratings(Note 3)

Supply Voltage
V_{CC} −0.5V to + 7.0V
Input Voltage (V_I) (Note 4)
A_1–A_{13}, PLH_{IN}, DIR, HD −0.5V to V_{CC} + 0.5V
B_1–B_8, C_{14}–C_{17}, HLH_{IN} −0.5V to + 5.5V (DC)
B_1–B_8, C_{14}–C_{17}, HLH_{IN} −2.0V to + 7.0V *
*40 ns Transient
Output Voltage (V_O)
A_1–A_8, A_{14}–A_{17}, HLH −0.5V to V_{CC} + 0.5V
B_1–B_8, Y_9–Y_{13}, PLH −0.5V to + 5.5V (DC)
B_1–B_8, Y_9–Y_{13}, PLH −2.0V to + 7.0V*
*40 ns Transient
DC Output Current (I_O)
A_1–A_8, HLH ±25 mA
B_1–B_8, Y_9–Y_{13} ±50 mA
PLH (Output LOW) 84 mA
PLH (Output HIGH) −50 mA
Input Diode Current (I_{IK}) (Note 4)
DIR, HD, A_9–A_{13},
PLH, HLH, C_{14}–C_{17} −20 mA
Output Diode Current (I_{OK})
A_1–A_8, A_{14}–A_{17}, HLH ±50 mA
B_1–B_8, Y_9–Y_{13}, PLH −50 mA
DC Continuous V_{CC} or
Ground Current ±200 mA
Storage Temperature −65°C to + 150°C
ESD (HBM) Last Passing
Voltage 2000V

Recommended Operating Conditions

Supply Voltage
V_{CC} 4.5V to 5.5V
DC Input Voltage (V_I) 0V to V_{CC}
Open Drain Voltage (V_O) 0V to 5.5V
Operating Temperature (T_A) −40°C to + 85°C

Note 3: Absolute Maximum continuos ratings are those values beyond which damage to the device may occur. Exposure to these indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		V_{CC} (V)	T_A = −40°C to +85°C Guaranteed Limits	Units	Conditions
V_{IK}	Input Clamp Diode Voltage		3.0	−1.2	V	I_I = −18 mA
V_{IH}	Minimum HIGH Level Input Voltage	A_n, PLH_{IN}, DIR, HD	4.5 – 5.5	0.7 V_{CC}	V	
		B_n	4.5 – 5.5	2.0		
		C_n	4.5 – 5.5	2.3		
		HLH_{IN}	4.5 – 5.5	2.6		
V_{IL}	Maximum LOW Level Input Voltage	A_n, PLH_{IN}, DIR, HD	4.5 – 5.5	0.3 V_{CC}	V	
		B_n	4.5 – 5.5	0.8		
		C_n	4.5 – 5.5	0.8		
		HLH_{IN}	4.5 – 5.5	1.6		
ΔVT	Minimum Input Hysteresis	A_n, PLH_{IN}, DIR, HD	4.5 – 5.5	0.4	V	V_T^+–V_T^-
		B_n	4.5 – 5.5	0.4		V_T^+–V_T^-
		C_n	5.0	0.8		V_T^+–V_T^-
		HLH_{IN}	5.0	0.3		V_T^+–V_T^-
V_{OH}	Minimum HIGH Level Output Voltage	A_n, HLH	4.5	4.4	V	I_{OH} = −50 μA
			4.5	3.8		I_{OH} = −8 mA
		B_n, Y_n	4.5	3.73		I_{OH} = −14 mA
		PLH	4.5	4.45		I_{OH} = −500 μA
V_{OL}	Maximum LOW Level Output Voltage	A_n, HLH	4.5	0.1	V	I_{OL} = 50 μA
			4.5	0.44		I_{OL} = 8 mA
		B_n, Y_n	4.5	0.77		I_{OL} = 14 mA
		PLH	4.5	0.7		I_{OL} = 84 mA
RD	Maximum Output Impedance	B_1–B_8, Y_9–Y_{13}	5.0	55	Ω	(Note 5)(Note 6)
	Minimum Output Impedance	B_1–B_8, Y_9–Y_{13}	5.0	35	Ω	(Note 5)(Note 6)
RP	Maximum Pull-Up Resistance	B_1–B_8, Y_9–Y_{13}, C_{14}–C_{17}	5.0	1650	Ω	
	Minimum Pull-Up Resistance	B_1–B_8, Y_9–Y_{13}, C_{14}–C_{17}	5.0	1150	Ω	
I_{IH}	Maximum Input Current in HIGH State	A_9–A_{13}, PLH_{IN}, HD, DIR, HLH_{IN}	5.5	1.0	μA	V_I = 5.5V
		C_{14}–C_{17}	5.5	100		V_I = 5.5V

DC Electrical Characteristics (Continued)

Symbol	Parameter		V_{CC} (V)	$T_A = -40°C$ to $+85°C$ Guaranteed Limits	Units	Conditions
I_{IL}	Maximum Input Current in LOW State	A_9–A_{13}, PLH_{IN}, HD, DIR, HLH_{IN}	5.5	−1.0	µA	$V_I = 0.0V$
		C_{14}–C_{17}	5.5	−5.0	mA	$V_I = 0.0V$
I_{OZH}	Maximum Output Disable Current (HIGH)	A_1—A_8	5.5	20	µA	$V_O = 5.5V$
		B_1–B_8	5.5	100		$V_O = 5.5V$
I_{OZL}	Maximum Output Disable Current (LOW)	A_1—A_8	5.5	−20	µA	$V_O = 0.0V$
		B_1–B_8	5.5	−5.0	mA	
I_{OFF}	Power Down Output Leakage	B_1–B_8, Y_9–Y_{13}, PLH	0.0	100	µA	$V_O = 5.5V$
I_{OFF}	Power Down Input Leakage	C_{14}–C_{17}, HLH_{IN}	0.0	100	µA	$V_I = 5.5V$
$I_{OFF} - I_{CC}$	Power Down Leakage to V_{CC}		0.0	250	µA	(Note 7)
I_{CC}	Maximum Supply Current		5.5	70	mA	$V_I = V_{CC}$ or GND

Note 5: Output impedance is measured with the output active LOW and active HIGH (HD = HIGH).

Note 6: This parameter is guaranteed but not tested, characterized only.

Note 7: Power-down leakage to V_{CC} is tested by simultaneously forcing all pins on the cable-side (B_1–B_8, Y_9–Y_{13}, PLH, C_{14}–C_{17} and HLH_{IN} to 5.5V and measuring the resulting I_{CC}.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V - 5.5V$		Units	Fig. No.
		Min	Max		
t_{PHL}	$A_1–A_8$ to $B_1–B_8$	2.0	30.0	ns	Figure 1
t_{PLH}	$A_1–A_8$ to $B_1–B_8$	2.0	30.0	ns	Figure
t_{PHL}	$B_1–B_8$ to $A_1–A_8$	2.0	30.0	ns	Figure 3
t_{PLH}	$B_1–B_8$ to $A_1–A_8$	2.0	30.0	ns	Figure 3
t_{PHL}	$A_9–A_{13}$ to $Y_9–Y_{13}$	2.0	30.0	ns	Figure 1
t_{PLH}	$A_9–A_{13}$ to $Y_9–Y_{13}$	2.0	30.0	ns	Figure
t_{PHL}	$C_{14}–C_{17}$ to $A_{14}–A_{17}$	2.0	30.0	ns	Figure 3
t_{PLH}	$C_{14}–C_{17}$ to $A_{14}–A_{17}$	2.0	30.0	ns	Figure 3
t_{SKEW}	LH-LH or HL-HL		6.0	ns	(Note 9)
t_{PHL}	PLH_{IN} to PLH	2.0	30.0	ns	Figure 1
t_{PLH}	PLH_{IN} to PLH	2.0	30.0	ns	Figure
t_{PHL}	HLH_{IN} to HLH	2.0	30.0	ns	Figure 3
t_{PLH}	HLH_{IN} to HLH	2.0	30.0	ns	Figure 3
t_{PHZ}	Output Disable Time	2.0	18.0	ns	Figure 7
t_{PLZ}	DIR to $A_1–A_8$	2.0	18.0		
t_{PZH}	Output Enable Time	2.0	25.0	ns	Figure 8
t_{PZL}	DIR to $A_1–A_8$	2.0	25.0		
t_{PHZ}	Output Disable Time	2.0	25.0	ns	Figure 9
t_{PLZ}	DIR to $B_1–B_8$	2.0	25.0		
t_{pEN}	Output Enable Time	2.0	28.0	ns	Figure
	HD to $B_1–B_8$, $Y_9–Y_{13}$				
t_{pDis}	Output Disable Time	2.0	28.0	ns	Figure
	HD to $B_1–B_8$, $Y_9–Y_{13}$				
$t_{pEn}–t_{pDis}$	Output Enable-Output Disable		20.0	ns	
t_{SLEW}	Output Slew Rate				
t_{PLH}	$B_1–B_8$, $Y_9–Y_{13}$	0.05	0.40	V/ns	Figure 5
t_{PHL}		0.05	0.40		Figure 4
t_r, t_f	t_{RISE} and t_{FALL}		120	ns	Figure 6
	$B_1–B_8$, $Y_9–Y_{13}$ (Note 8)		120		(Note 10)

Note 8: Open Drain

Note 9: t_{SKEW} is measured for common edge output transitions and compares the measured propagation delay for a given path type.

(i) $A_1–A_8$ to $B_1–B_8$, $A_9–Y_{13}$ to $Y_9–Y_{13}$

(ii) $B_1–B_8$ to $A_1–A_8$

(iii) $C_{14}–C_{17}$ to $A_{14}–A_{17}$

Note 10: This parameter is guaranteed but not tested, characterized only.

Note 11: Pulse Generator for all pulses: Rate ≤ 1.0 MHz; $Z_O \leq 50\Omega$; $t_f \leq 2.5$ ns, $t_r \leq 2.5$ ns.

Capacitance (Note 12)

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0.0V$ (HD, DIR, A_9—A_{13}, C_{14}—C_{17}, PLH_{IN} and HLH_{IN})
$C_{I/O}$	I/O Pin Capacitance	12	pF	$V_{CC} = 3.3V$

Note 12: Capacitance is measured at frequency = 1 MHz.

AC Loading and Waveforms

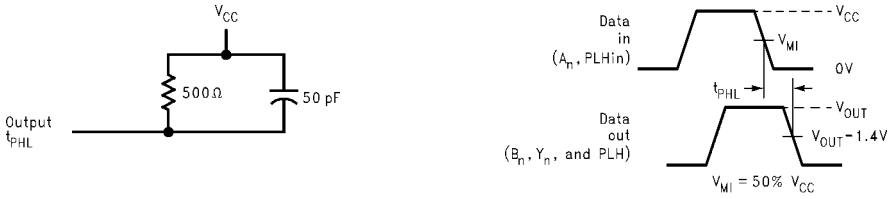


FIGURE 1. t_{PHL} Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}
PLH_{IN} to PLH

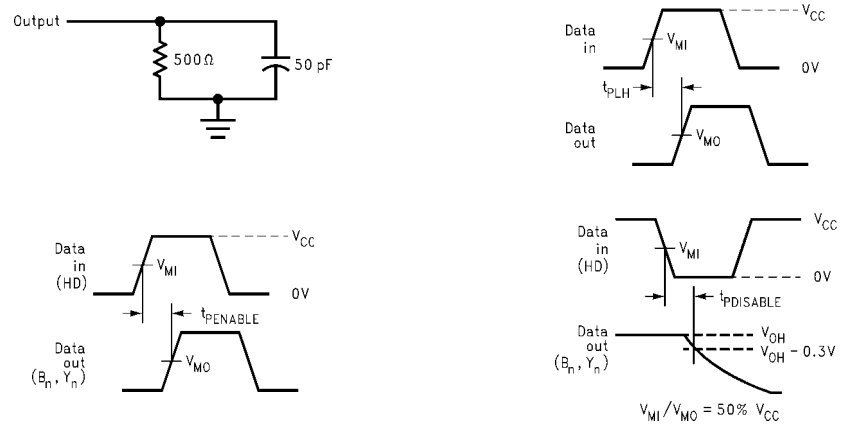


FIGURE 2. t_{PLH}, t_{pEn}, t_{pDis}Test Load and Waveforms
A_1–A_8 to B_1–B_8, A_9–A_{13} to Y_9–Y_{13}
PLH_{IN} to PLH, HD to B_1–B_8, Y_9–Y_{13}, PLH

FIGURE 3. t_{PHL}, t_{PLH} Test Load and Waveforms
B_1–B_8 to A_1–A_8, C_{14}–C_{17} to A_{14}–A_{17}, HLH_{IN} to HLH

AC Loading and Waveforms (Continued)

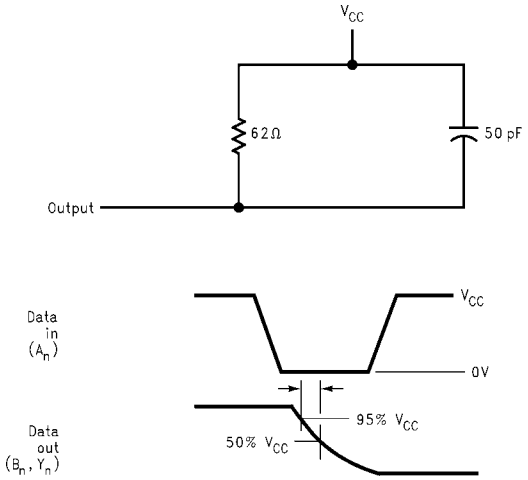


FIGURE 4. t_{SLEW} HL Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}

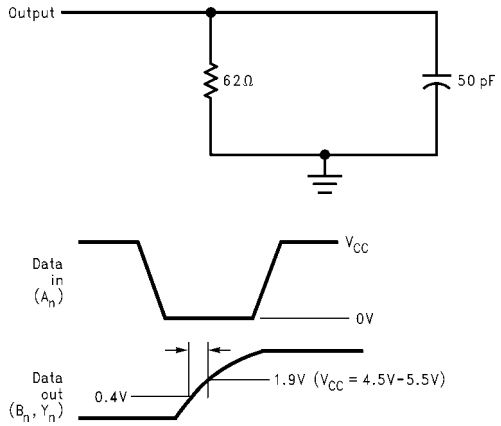
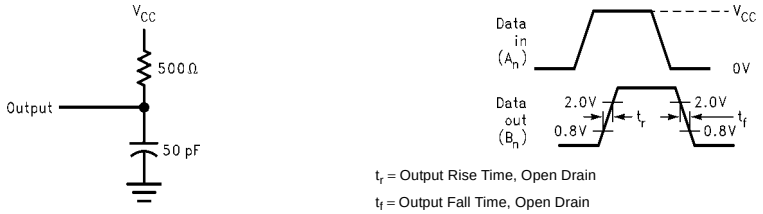


FIGURE 5. t_{SLEW} LH Test Load and Waveforms
A_1–A_8 to B_1–B_8
A_9–A_{13} to Y_9–Y_{13}



t_r = Output Rise Time, Open Drain

t_f = Output Fall Time, Open Drain

FIGURE 6. t_{RISE} and t_{FALL} Test Load and Waveforms for Open Drain Outputs
A_1–A_8 to B_1–B_8, A_9–A_{13} to Y_9–Y_{13}

AC Loading and Waveforms (Continued)

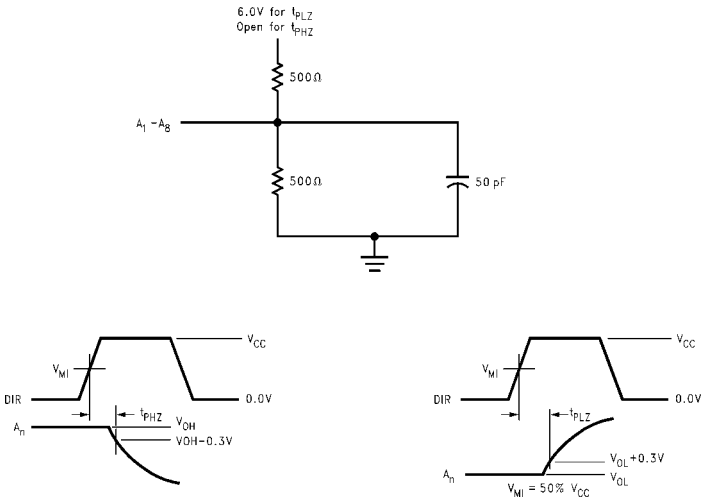


FIGURE 7. t_{PHZ} and t_{PLZ} Test Load and Waveforms, DIR to A_1–A_8

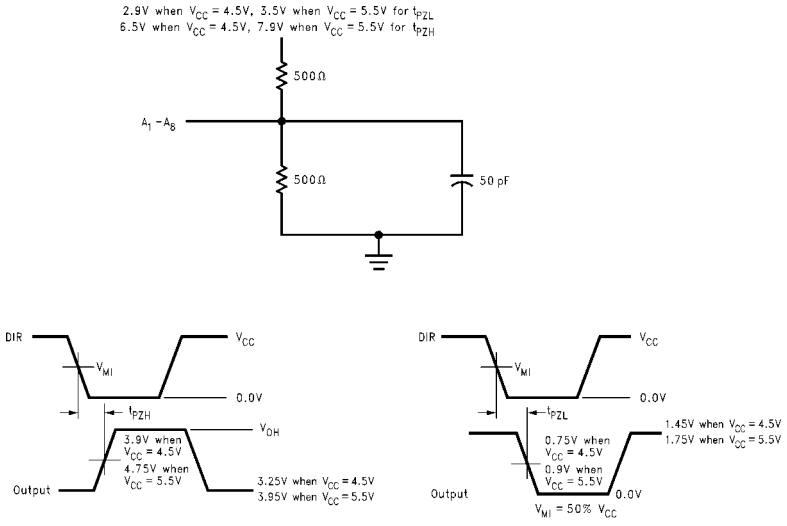


FIGURE 8. t_{PZH} and t_{PZL} Test Load and Waveforms, DIR to A_1–A_8

AC Loading and Waveforms (Continued)

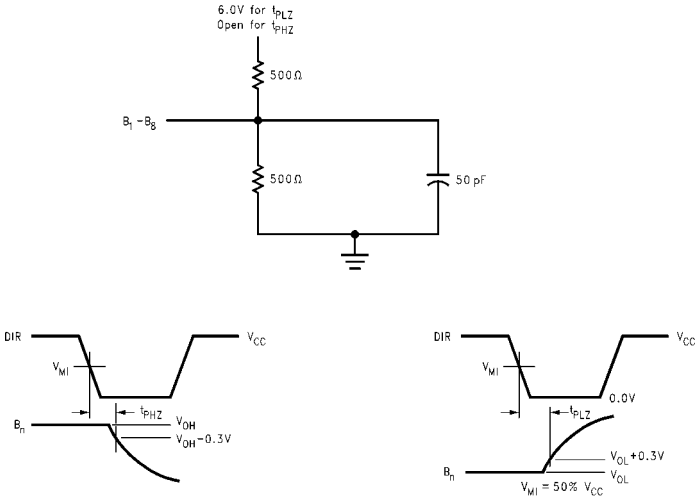
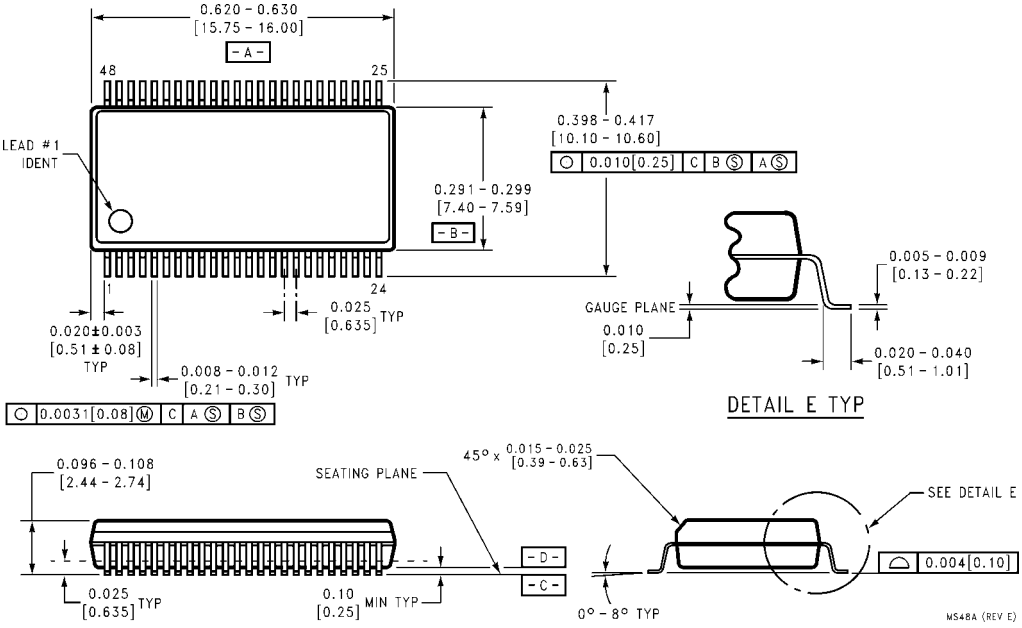


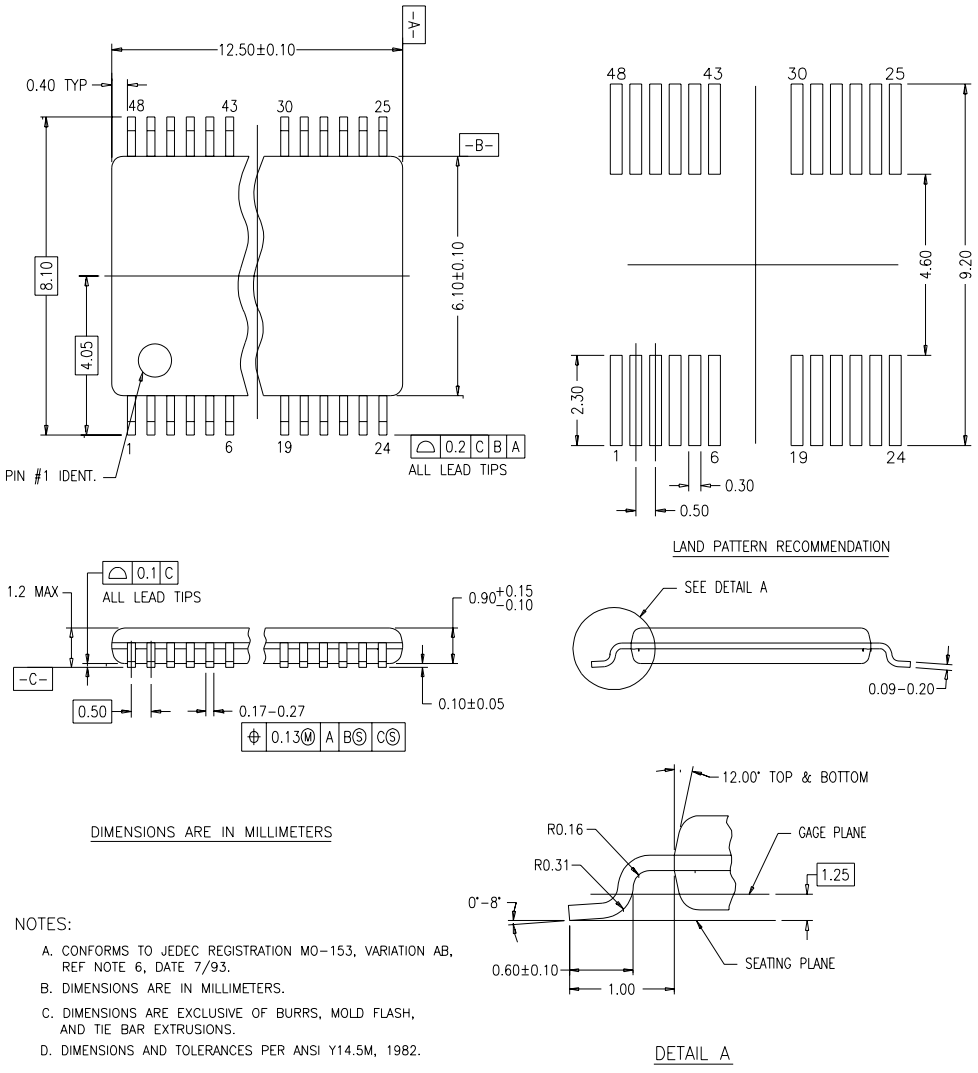
FIGURE 9. t_{PHZ} and t_{PLZ} Test Load and Waveforms, DIR to B_1–B_8

Physical Dimensions inches (millimeters) unless otherwise noted



48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300 Wide
Package Number MS48A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTD48REVB1

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD48

FAIRCHILD SEMICONDUCTOR™

September 1995
Revised April 1999

74VHC163
4-Bit Binary Counter with Synchronous Clear

General Description

The VHC163 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC163 is a high-speed synchronous modulo-16 binary counter. This device is synchronously presettable for application in programmable dividers and has two types of Count Enable inputs plus a Terminal Count output for versatility in forming multistage counters. The CLK input is active on the rising edge. Both $\overline{PE}$ and $\overline{MR}$ inputs are active on low logic level. Presetting is synchronous to rising edge of CLK and the Clear function of the VHC163 is synchronous to CLK. Two enable inputs (ENP and ENT) and Carry Output are provided to enable easy cascading of counters, which facilitates easy implementation of n-bit counters without using external gates.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

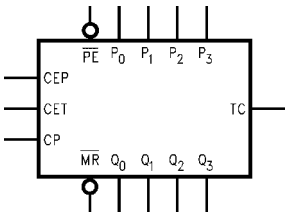
- High speed: f_{MAX} = 185 MHz (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- Synchronous counting and loading
- High-speed synchronous expansion
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC163

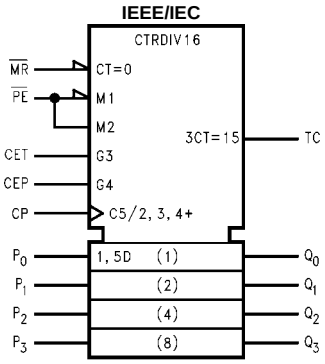
Ordering Code:

Order Number	Package Number	Package Description
74VHC163M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC163SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC163MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC163N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

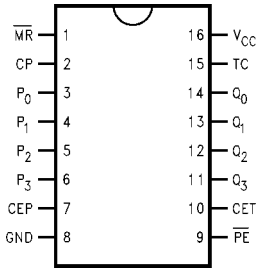
Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols





Connection Diagram



Pin Descriptions

Pin Names	Description
CEP	Count Enable Parallel Input
CET	Count Enable Trickle Input
CP	Clock Pulse Input
$\overline{MR}$	Synchronous Master Reset Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Inputs
Q_0–Q_3	Flip-Flop Outputs
TC	Terminal Count Output

Functional Description

The VHC163 counts in modulo-16 binary sequence. From state 15 (HHHH) it increments to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: synchronous reset, parallel load, count-up and hold. Four control inputs—Synchronous Reset ($\overline{MR}$), Parallel Enable ($\overline{PE}$), Count Enable Parallel (CEP) and Count Enable Trickle (CET)—determine the mode of operation, as shown in the Mode Select Table. A LOW signal on $\overline{MR}$ overrides counting and parallel loading and allows all outputs to go LOW on the next rising edge of CP. A LOW signal on $\overline{PE}$ overrides counting and allows information on the Parallel Data (P_n) inputs to be loaded into the flip-flops on the next rising edge of CP. With $\overline{PE}$ and $\overline{MR}$ HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The VHC163 uses D-type edge-triggered flip-flops and changing the $\overline{MR}$, $\overline{PE}$, CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 15. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to TC delay of the first stage, plus the cumulative CET to TC delays of the intermediate stages, plus the CET to CP setup time of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in Figure 2 are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle takes 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to TC delay of the first stage plus the CEP to CP setup time of the last stage. The TC output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters.

Logic Equations: Count Enable = CEP • CET • $\overline{PE}$

$TC = Q_0 \cdot Q_1 \cdot Q_2 \cdot Q_3 \cdot CET$

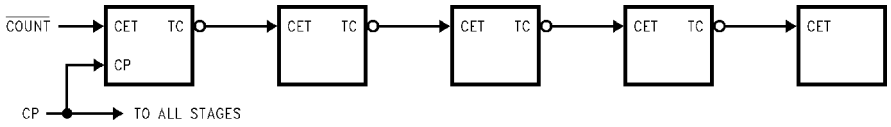


FIGURE 1.

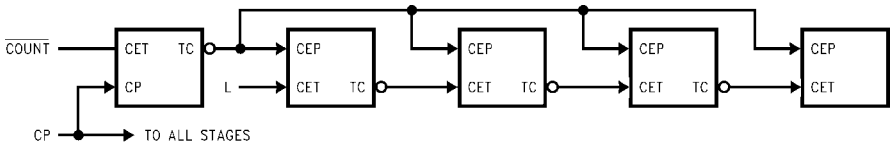


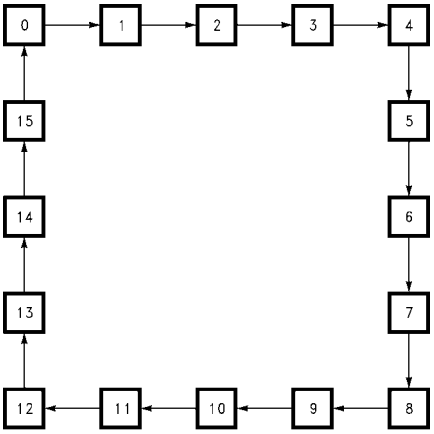
FIGURE 2.

Mode Select Table

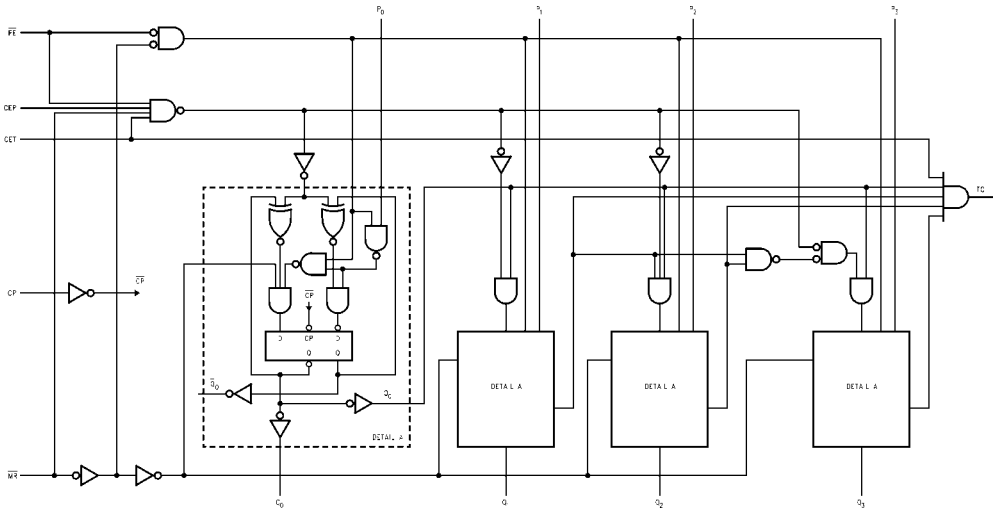
$\overline{MR}$	$\overline{PE}$	CET	CEP	Action on the Rising Clock Edge (⌒)
L	X	X	X	Reset (Clear)
H	L	X	X	Load ($P_n \rightarrow Q_n$)
H	H	H	H	Count (Increment)
H	H	L	X	No Change (Hold)
H	H	X	L	No Change (Hold)

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagram



Block Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.50		0.50	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9			or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1		or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay Time ($CP–Q_n$)	3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	C_L = 15 pF
				10.8	16.3	1.0	18.5		C_L = 50 pF
		5.0 ± 0.5		4.9	8.1	1.0	9.5	ns	C_L = 15 pF
				6.4	10.1	1.0	11.5		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP–TC, Count)	3.3 ± 0.3		8.7	13.6	1.0	16.0	ns	C_L = 15 pF
				11.2	17.1	1.0	19.5		C_L = 50 pF
		5.0 ± 0.5		4.9	8.1	1.0	9.5	ns	C_L = 15 pF
				6.4	10.1	1.0	11.5		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP–TC, Load)	3.3 ± 0.3		11.0	17.2	1.0	20.0	ns	C_L = 15 pF
				13.5	20.7	1.0	23.5		C_L = 50 pF
		5.0 ± 0.5		6.2	10.3	1.0	12.0	ns	C_L = 15 pF
				7.7	12.3	1.0	14.0		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CET–TC)	3.3 ± 0.3		7.5	12.3	1.0	14.5	ns	C_L = 15 pF
				10.5	15.8	1.0	18.0		C_L = 50 pF
		5.0 ± 0.5		4.9	8.1	1.0	9.5	ns	C_L = 15 pF
				6.4	10.1	1.0	11.5		C_L = 50 pF
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	80	130		70		MHz	C_L = 15 pF
			55	85		50			C_L = 50 pF
		5.0 ± 0.5	135	185		115		MHz	C_L = 15 pF
			95	125		85			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			23				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

When the outputs drive a capacitive load, total current consumption is the sum of C_{PD}, and ΔI_{CC} which is obtained from the following formula:

$$\Delta I_{CC} = F_{CP} \bullet V_{CC} \left(\frac{C_{Q0}}{2} + \frac{C_{Q1}}{4} + \frac{C_{Q2}}{8} + \frac{C_{Q3}}{16} + \frac{C_{TC}}{16} \right)$$

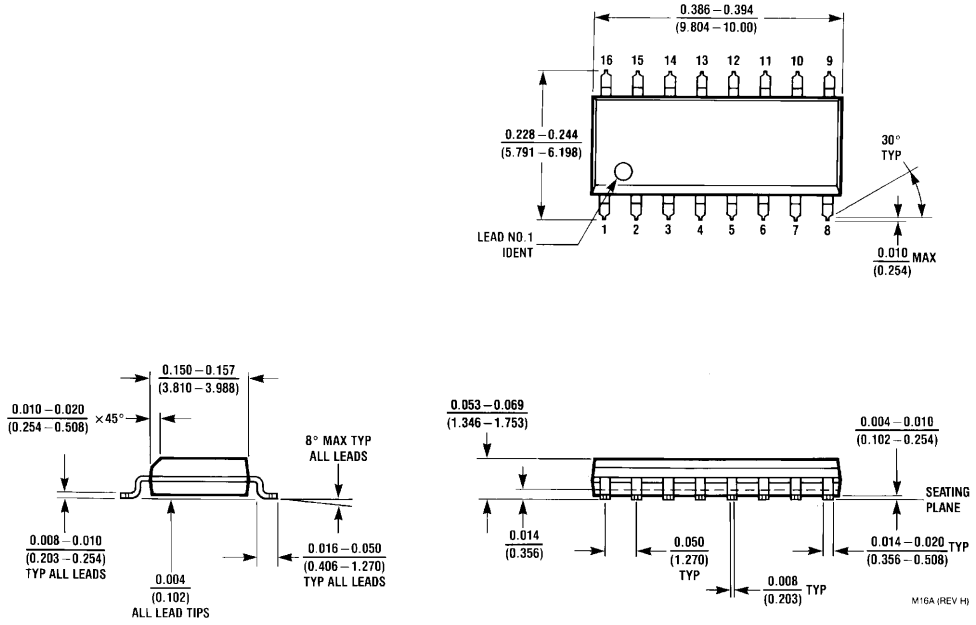
C_{Q0}–C_{Q3} and C_{TC} are the capacitances at Q0–Q3 and TC, respectively. F_{CP} is the input frequency of the CP.

AC Operating Requirements

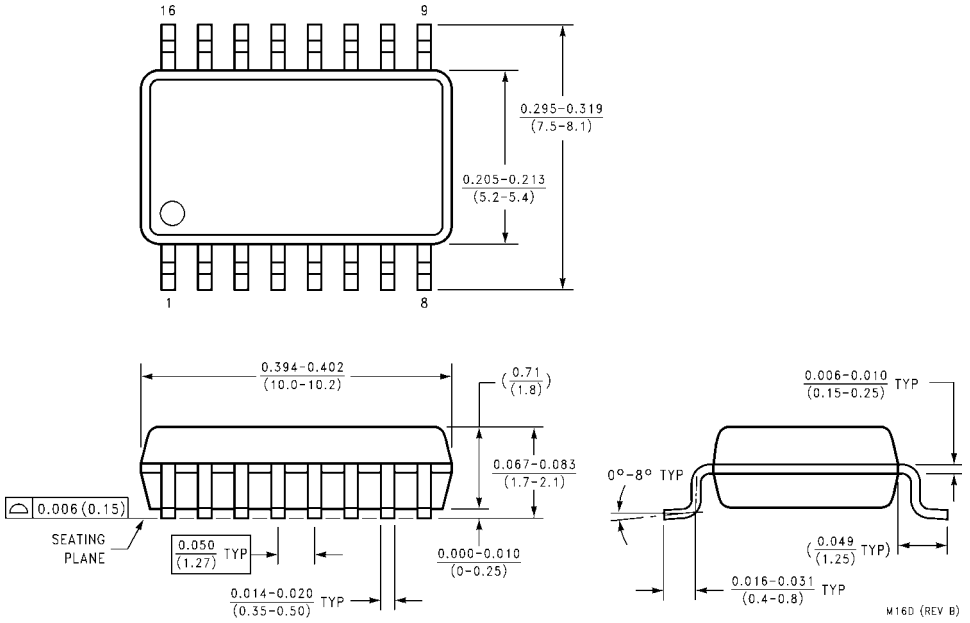
Symbol	Parameter	V_{CC} (Note 5) (V)	$T_A = 25°C$	$T_A = -40°C$	Units
			Typ	Guaranteed Minimum	
t_S	Minimum Setup Time	3.3	5.5	6.5	ns
	(P_n–CP)	5.0	4.5	4.5	
t_S	Minimum Setup Time	3.3	8.0	9.5	ns
	($\overline{PE}$ –CP)	5.0	5.0	6.0	
t_S	Minimum Setup Time	3.3	7.5	9.0	ns
	(CEP or CET–CP)	5.0	5.0	6.0	
t_S	Minimum Setup Time	3.3	4.0	4.0	ns
	($\overline{MR}$ –CP)	5.0	3.5	3.5	
t_H	Minimum Hold Time	3.3	1.0	1.0	ns
	(P_n–CP)	5.0	1.0	1.0	
t_H	Minimum Hold Time	3.3	1.0	1.0	ns
	($\overline{PE}$ –CP)	5.0	1.0	1.0	
t_H	Minimum Hold Time	3.3	1.0	1.0	ns
	(CEP or CET–CP)	5.0	1.0	1.0	
t_H	Minimum Hold Time	3.3	1.0	1.0	ns
	($\overline{MR}$ –CP)	5.0	1.5	1.5	
$t_W(L)$	Minimum Pulse Width	3.3	5.0	5.0	ns
$t_W(H)$	CP (Count)	5.0	5.0	5.0	

Note 5: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

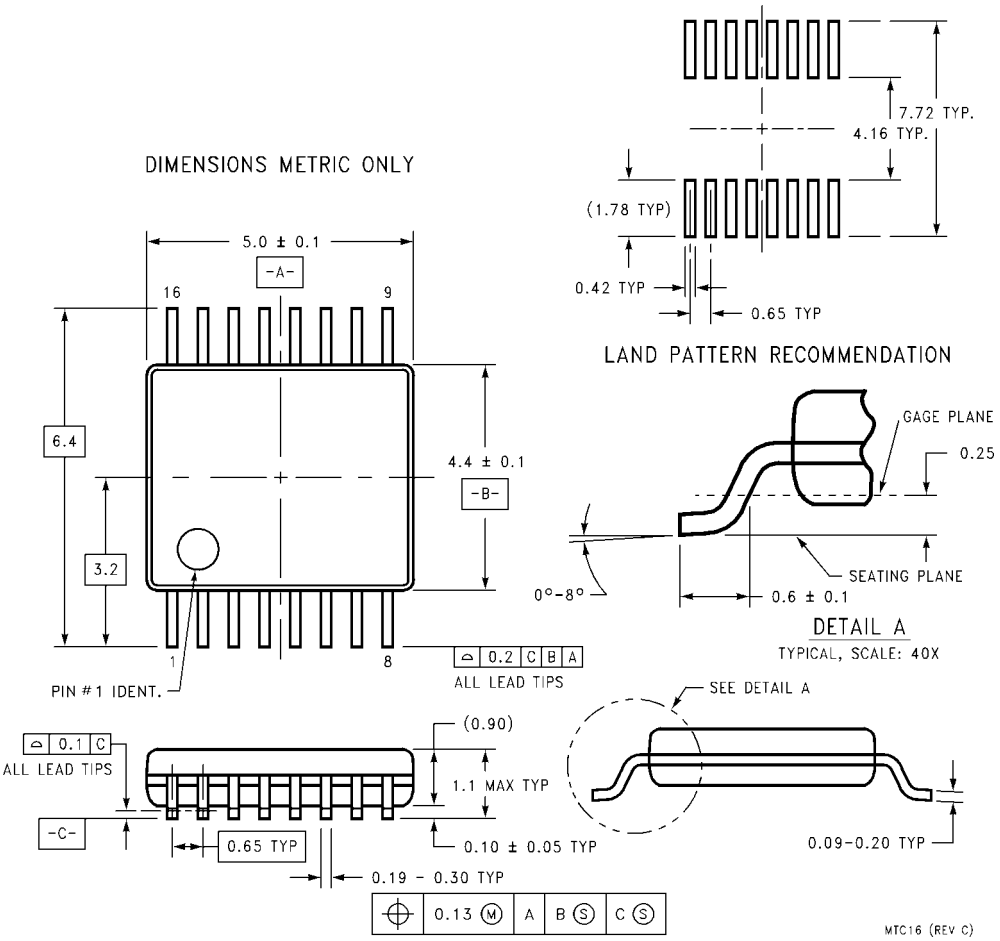


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



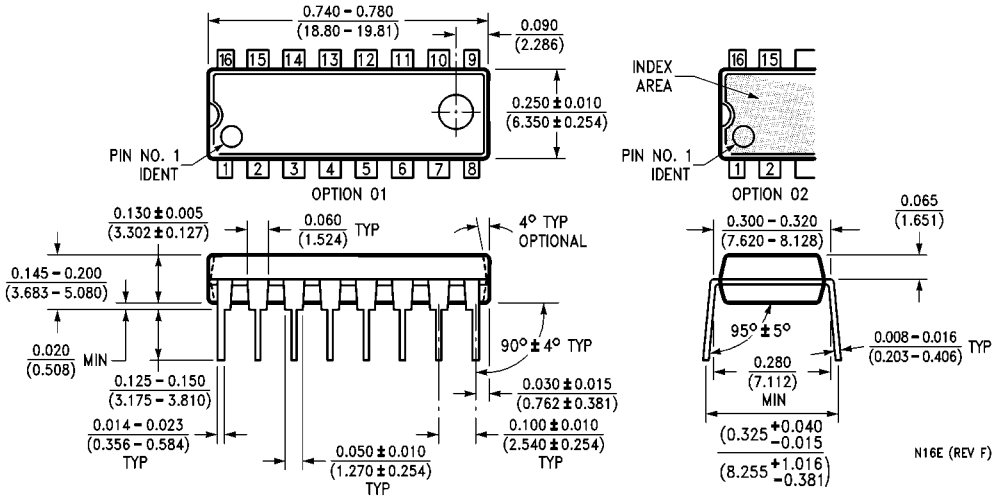
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised April 1999

74VHC164
8-Bit Serial-In, Parallel-Out Shift Register

General Description

The VHC164 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC164 is a high-speed 8-Bit Serial-In/Parallel-Out Shift Register. Serial data is entered through a 2-input AND gate synchronous with the LOW-to-HIGH transition of the clock. The device features an asynchronous Master Reset which clears the register, setting all outputs LOW independent of the clock. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

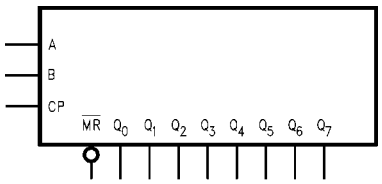
- High Speed: f_{MAX} = 175 MHz at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC164

Ordering Code:

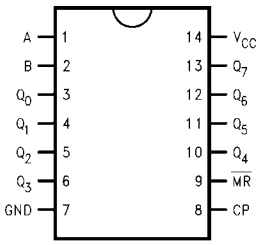
Order Number	Package Number	Package Description
74VHC164M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHC164SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC164MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC164N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A, B	Data Inputs
CP	Clock Pulse Input (Active Rising Edge)
$\overline{MR}$	Master Reset Input (Active LOW)
Q_0–Q_7	Outputs

Functional Description

The VHC164 is an edge-triggered 8-bit shift register with serial data entry and an output from each of the eight stages. Data is entered serially through one of two inputs (A or B); either of these inputs can be used as an active High Enable for data entry through the other input. An unused input must be tied HIGH.

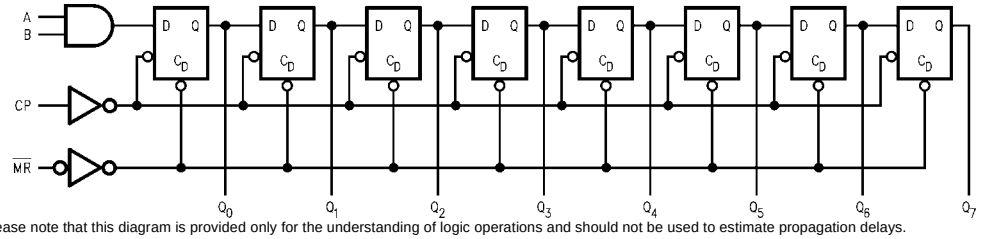
Each LOW-to-HIGH transition on the Clock (CP) input shifts data one place to the right and enters into Q_0 the logical AND of the two data inputs (A • B) that existed before the rising clock edge. A LOW level on the Master Reset ($\overline{MR}$) input overrides all other inputs and clears the register asynchronously, forcing all Q outputs LOW.

Function Table

Operating Mode	Inputs			Outputs	
	$\overline{MR}$	A	B	Q_0	Q_1–Q_7
Reset (Clear)	L	X	X	L	L–L
Shift	H	L	L	L	Q_0–Q_6
	H	L	H	L	Q_0–Q_6
	H	H	L	L	Q_0–Q_6
	H	H	H	H	Q_0–Q_6

H = HIGH Voltage Levels
L = LOW Voltage Levels
X = Immaterial
Q = Lower case letters indicate the state of the referenced input or output one setup time prior to the LOW-to-HIGH clock transition.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to + 7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
DC Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of circuits outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0– 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	80	125		65		MHz	C_L = 15 pF
			50	75		45			C_L = 50 pF
		5.0 ± 0.5	125	175		105		MHz	C_L = 15 pF
			85	115		75			C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.4	12.8	1.0	15.0	ns	C_L = 15 pF
t_{PHL}	Time (CP–Q_n)			10.9	16.3	1.0	18.5		C_L = 50 pF
		5.0 ± 0.5		5.8	9.0	1.0	10.5	ns	C_L = 15 pF
				7.3	11.0	1.0	12.5		C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	C_L = 15 pF
t_{PHL}	Time ($\overline{MR}$–Q_n)			10.8	16.3	1.0	18.5		C_L = 50 pF
		5.0 ± 0.5		5.2	8.6	1.0	10.0	ns	C_L = 15 pF
				6.7	10.6	1.0	12.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			76				pF	(Note 4)

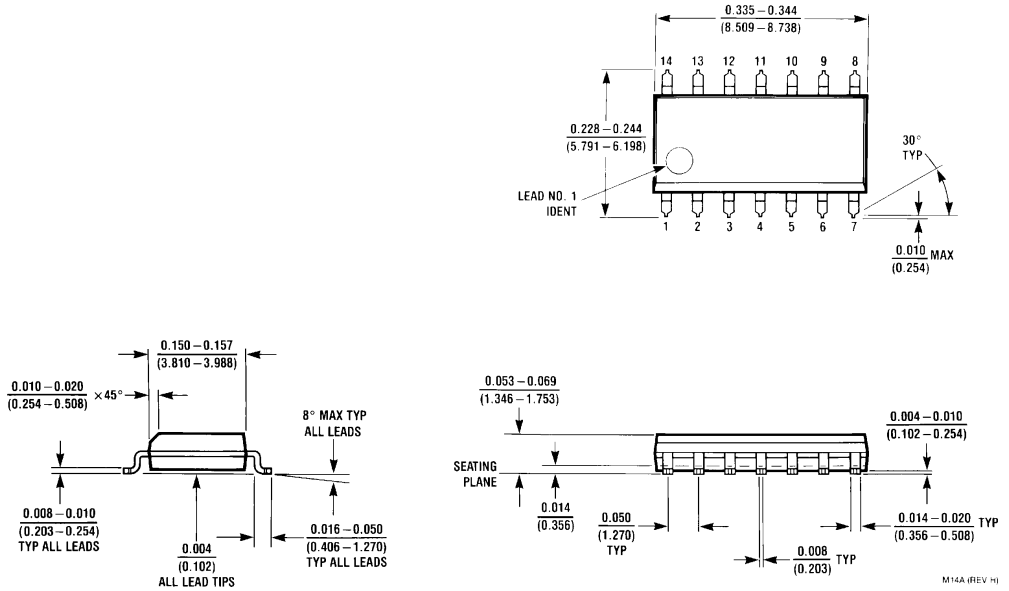
Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

AC Operating Requirements

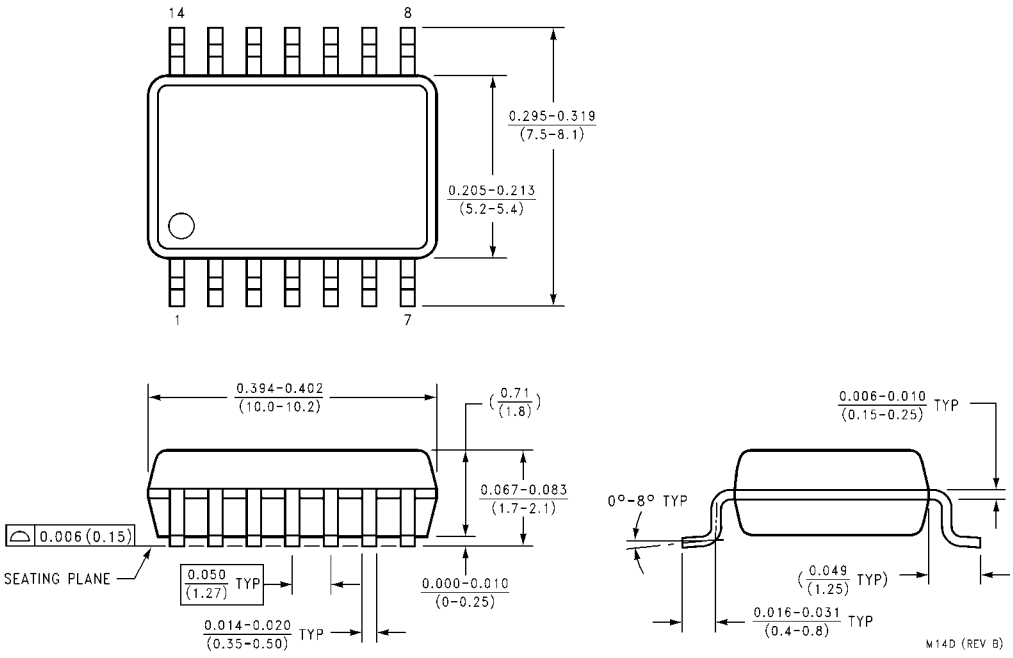
Symbol	Parameter	V_{CC} (V) (Note 5)	T_A = 25°C	T_A = −40°C to +85°C		Units
			Typ	Guaranteed Minimum		
t_W(L)	Minimum Pulse Width (CP)	3.3		5.0	5.0	ns
t_W(H)		5.0		5.0	5.0	
t_W(L)	Minimum Pulse Width ($\overline{MR}$)	3.3		5.0	5.0	ns
		5.0		5.0	5.0	
t_S	Minimum Setup Time	3.3		5.0	6.0	ns
		5.0		4.5	4.5	
t_H	Minimum Hold Time	3.3		0.0	0.0	ns
		5.0		1.0	1.0	
t_{REC}	Minimum Removal Time ($\overline{MR}$)	3.3		2.5	2.5	ns
		5.0		2.5	2.5	

Note 5: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

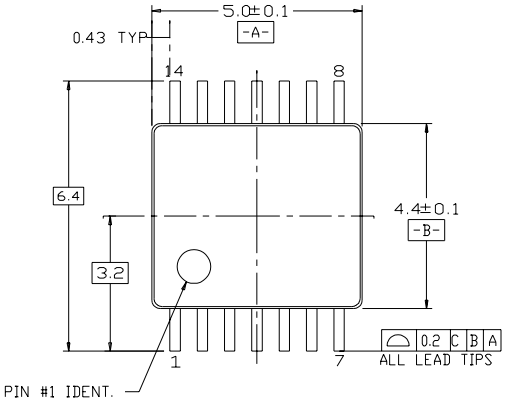


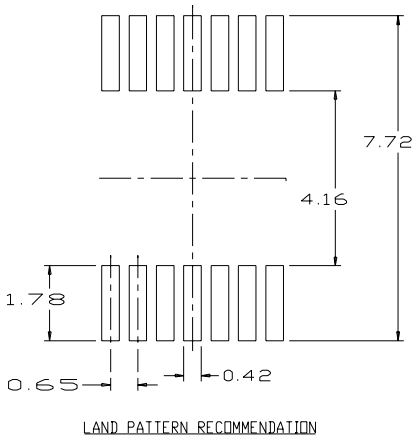
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

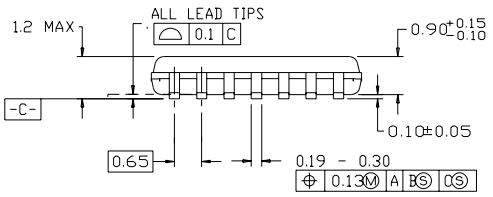


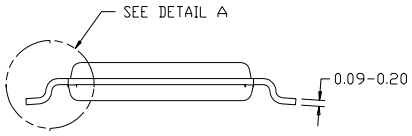
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

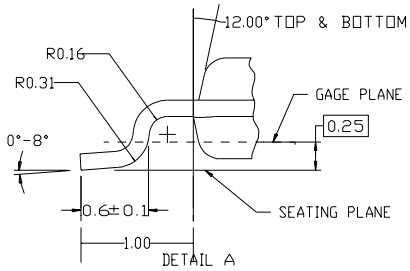
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)











NOTES:

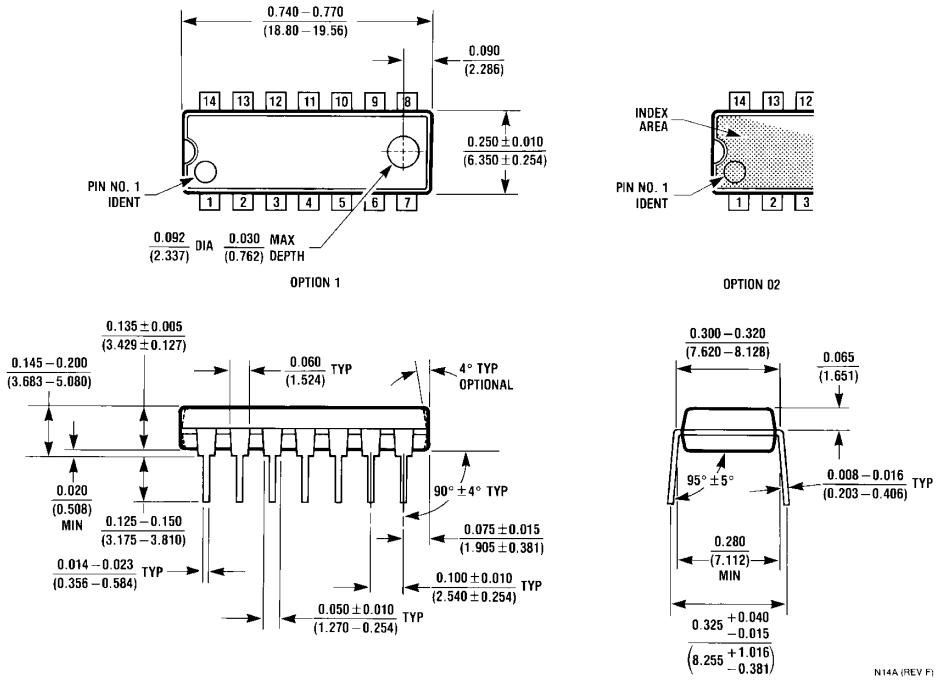
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised April 1999

74VHC175
Quad D-Type Flip-Flop

General Description

The VHC175 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC175 is a high-speed quad D-type flip-flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D inputs is stored during the LOW-to-HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D inputs, when LOW.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

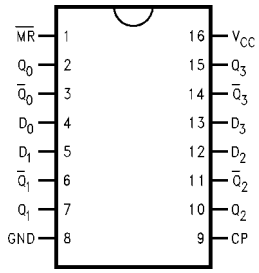
- High Speed: f_{MAX} = 210 MHz (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC175

Ordering Code:

Order Number	Package Number	Package Description
74VHC175M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC175SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC175MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC175N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

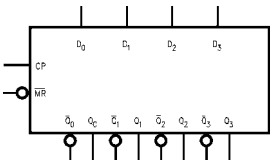
Connection Diagram



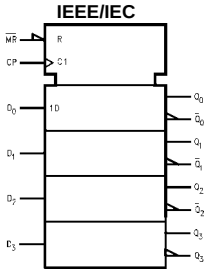
Pin Descriptions

Pin Names	Description
D_0–D_3	Data Inputs
CP	Clock Pulse Input
$\overline{MR}$	Master Reset Input
Q_0–Q_3	True Outputs
$\overline{Q}_0$–$\overline{Q}_3$	Complement Outputs

Logic Symbols



IEEE/IEC



Functional Description

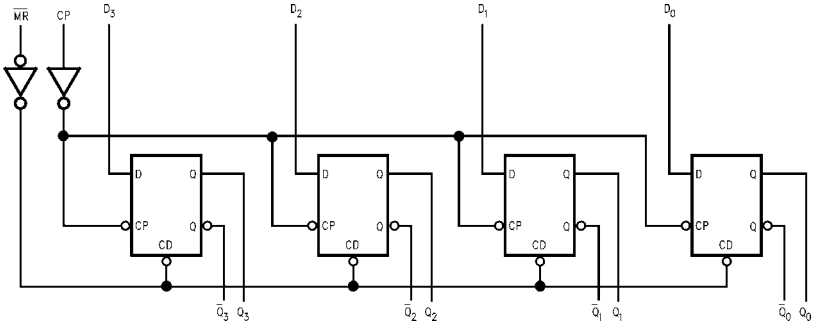
The VHC175 consists of four edge-triggered D flip-flops with individual D inputs and Q and $\overline{Q}$ outputs. The Clock and Master Reset are common. The four flip-flops will store the state of their individual D inputs on the LOW-to-HIGH clock (CP) transition, causing individual Q and $\overline{Q}$ outputs to follow. A LOW input on the Master Reset ($\overline{MR}$) will force all Q outputs LOW and $\overline{Q}$ outputs HIGH independent of Clock or Data inputs. The VHC175 is useful for general logic applications where a common Master Reset and Clock are acceptable.

Truth Table

Inputs	Outputs	
@ t_n, $\overline{MR}$ = H	@ t_{n+1}	
D_n	Q_n	$\overline{Q}_n$
L	L	H
H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
t_n = Bit Time before Clock Pulse
t_{n+1} = Bit Time after Clock Pulse

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	90	140		75		MHz	C_L = 15 pF
			50	75		45			C_L = 50 pF
		5.0 ± 0.5	150	210		125		MHz	C_L = 15 pF
			85	115		75			C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP to Q_n or $\overline{Q}_n$)	3.3 ± 0.3		7.5	11.5	1.0	13.5	ns	C_L = 15 pF
				10.0	15.0	1.0	17.0		C_L = 50 pF
		5.0 ± 0.5		4.8	7.3	1.0	8.5	ns	C_L = 15 pF
				6.3	9.3	1.0	10.5		C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{MR}$ to Q_n or $\overline{Q}_n$)	3.3 ± 0.3		6.3	10.1	1.0	12.0	ns	C_L = 15 pF
				8.8	13.6	1.0	15.5		C_L = 50 pF
		5.0 ± 0.5		4.3	6.4	1.0	7.5	ns	C_L = 15 pF
				5.8	8.4	1.0	9.5		C_L = 50 pF
t_{OSLH} t_{OSHL}	Output to Output Skew	3.3 ± 0.3			1.5		1.5		C_L = 50 pF
		5.0 ± 0.5			1.0		1.0		C_L = 50 pF (Note 4)
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			44				pF	(Note 5)

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

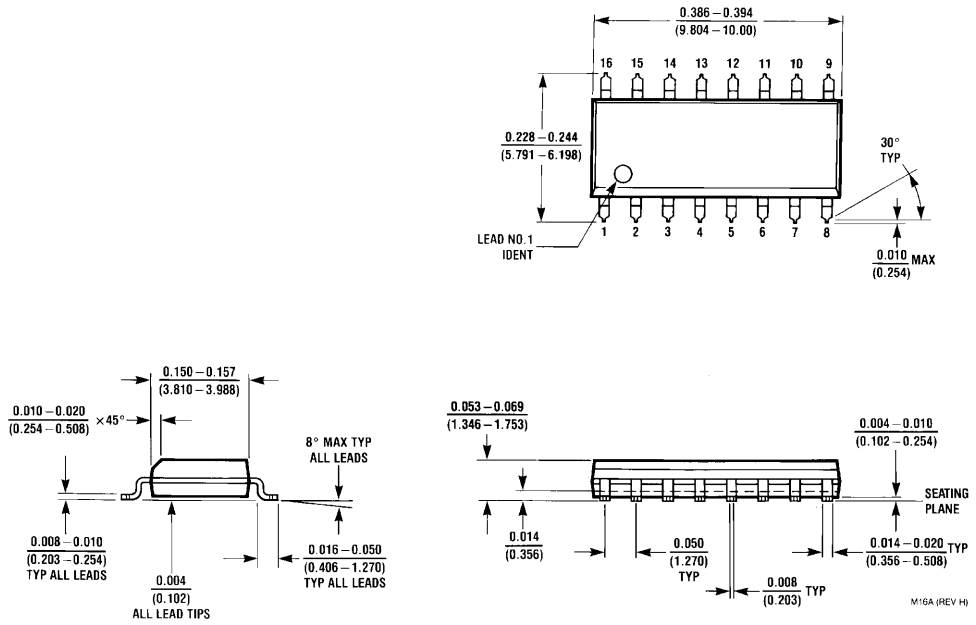
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/4$ (per F/F), and the total C_{PD} when n pcs of the Flip-Flop operate can be calculated by the following equation: C_{PD} (total) = 30 + 14 • n

AC Operating Requirements

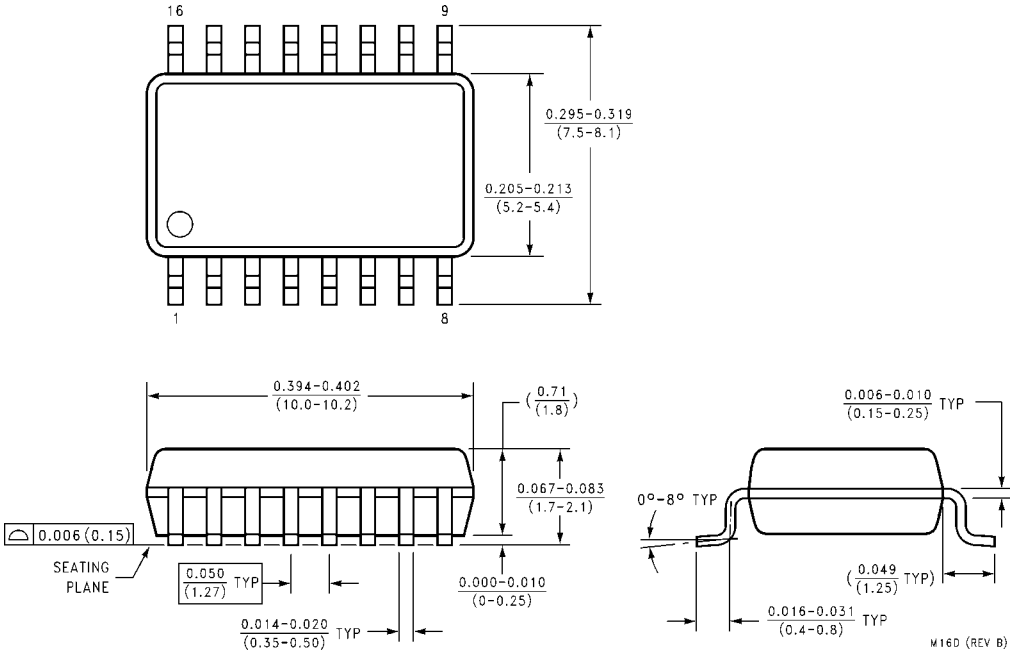
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
$t_W(L)$	Minimum Pulse Width (CP)	3.3		5.0	5.0	ns
$t_W(H)$		5.0		5.0	5.0	
$t_W(L)$	Minimum Pulse Width ($\overline{MR}$)	3.3		5.0	5.0	ns
		5.0		5.0	5.0	
t_S	Minimum Setup Time (Dn to CP)	3.3		5.0	5.0	ns
		5.0		4.0	4.0	
t_H	Minimum Hold Time (Dn to CP)	3.3		1.0	1.0	ns
		5.0		1.0	1.0	
t_{REC}	Minimum Removal Time ($\overline{MR}$)	3.3		5.0	5.0	ns
		5.0		5.0	5.0	

Note 6: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

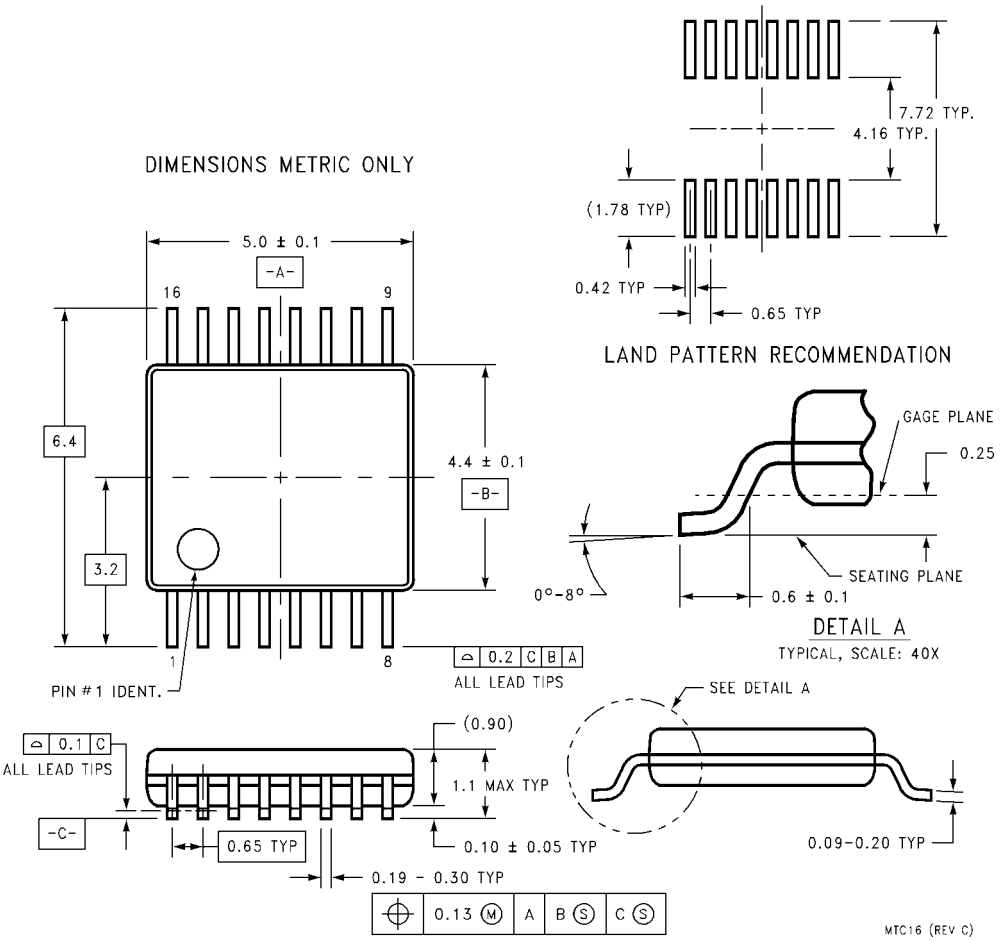


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



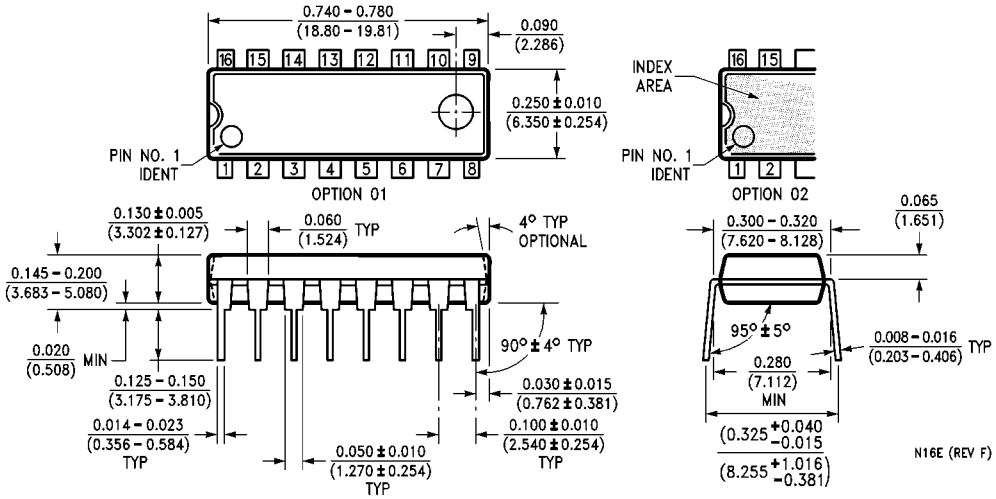
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1994
Revised May 1999

74VHC221A
Dual Non-Retriggerable Monostable Multivibrator

General Description

The VHC221A is an advanced high speed CMOS Monostable Multivibrator fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Each multivibrator features both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken LOW resets the one-shot. The VHC221A can be triggered on the positive transition of the clear while A is held LOW and B is held HIGH. The VHC221A is non-retriggerable, and therefore cannot be retriggered until the output pulse times out. The output pulse width is determined by the equation:

PW = (Rx)(Cx); where PW is in seconds, R is in ohms, and C is in farads.

Limits for R_x and C_x are:

External capacitor, C_x: No limit

External resistors, R_x: V_{CC}= 2.0V, 5 kΩ min

V_{CC} > 3.0V, 1 kΩ min

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

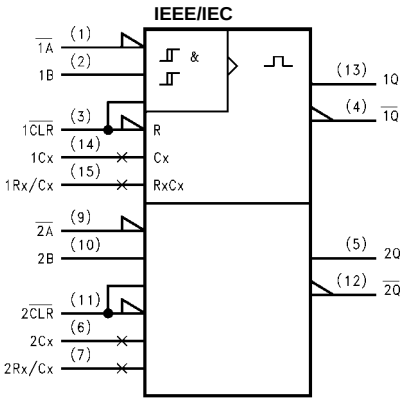
- High Speed: t_{PD} = 8.1 ns (typ) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 4 μA (Max) at T_A = 25°C
- Active State: I_{CC} = 600 μA (Max) at T_A = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC221A

Ordering Code:

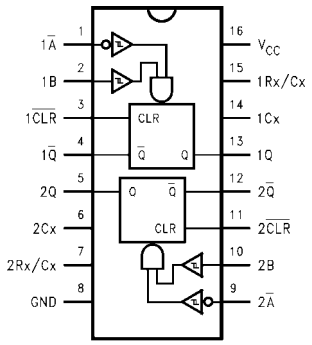
Order Number	Package Number	Package Description
74VHC221AM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC221ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC221AMTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC221AN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Truth Table

Inputs			Outputs		Function
$\overline{A}$	B	$\overline{CLR}$	Q	$\overline{Q}$	
↓	H	H	⎍	⎏	Output Enable
X	L	H	L	H	Inhibit
H	X	H	L	H	Inhibit
L	↑	H	⎍	⎏	Output Enable
L	H	↑	⎍	⎏	Output Enable
X	X	L	L	H	Reset

H = HIGH Voltage Level ↓ = HIGH-to-LOW Transition
L = LOW Voltage Level ↑ = LOW-to-HIGH Transition
X: Don't Care

Block Diagrams

Note A: Cx, Rx, Dx are external Capacitor, Resistor, and Diode, respectively.
Note B: External clamping diode, Dx;
External capacitor is charged to V_{CC} level in the wait state, i.e. when no trigger is applied.

If the supply voltage is turned off, Cx discharges mainly through the internal (parasitic) diode. If Cx is sufficiently large and V_{CC} drops rapidly, there will be some possibility of damaging the IC through in rush current or latch-up. If the capacitance of the supply voltage filter is large enough and V_{CC} drops slowly, the in rush current is automatically limited and damage to the IC is avoided.

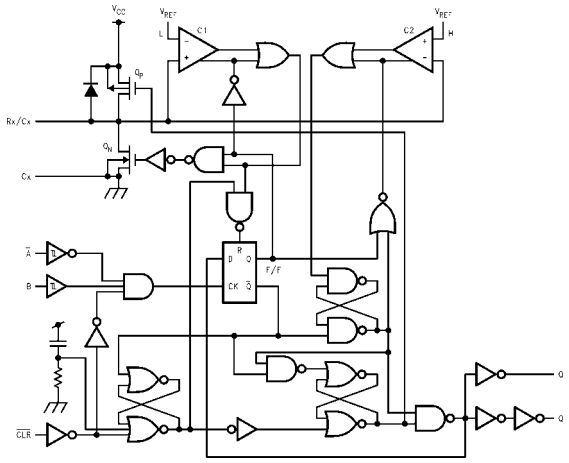
The maximum value of forward current through the parasitic diode is ±20 mA. In the case of a large Cx, the limit of fall time of the supply voltage is determined as follows:

$t_f \geq (V_{CC} - 0.7)\ Cx/20\ mA$

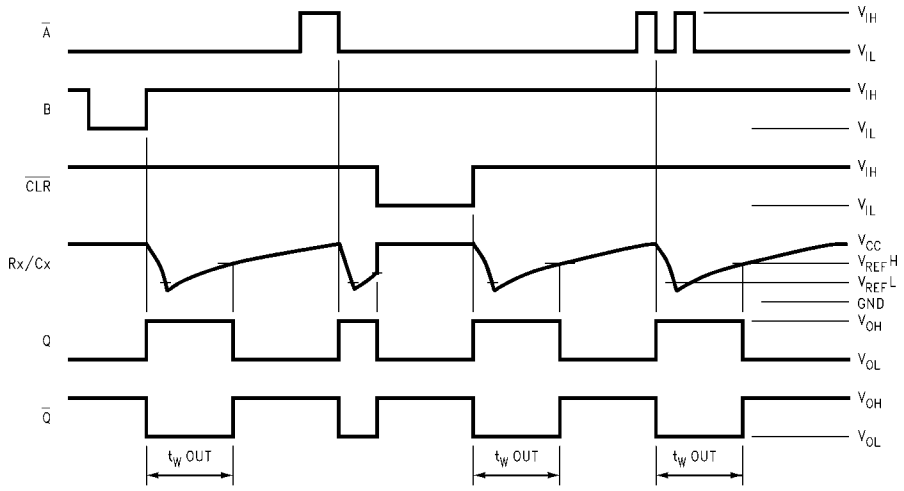
(t_f is the time between the supply voltage turn off and the supply voltage reaching 0.4 V_{CC})

In the event a system does not satisfy the above condition, an external clamping diode (Dx) is needed to protect the IC from rush current.

System Diagram



Timing Chart



Functional Description

1. Stand-by State

   The external capacitor (Cx) is fully charged to V_{CC} in the Stand-by State. That means, before triggering, the Q_P and Q_N transistors which are connected to the Rx/Cx node are in the off state. Two comparators that relate to the timing of the output pulse, and two reference voltage supplies turn off. The total supply current is only leakage current.

2. Trigger Operation

   Trigger operation is effective in any of the following three cases. First, the condition where the $\overline{A}$ input is LOW, and B input has a rising signal; second, where the B input is HIGH, and the A input has a falling signal; and third, where the $\overline{A}$ input is LOW and the B input is HIGH, and the $\overline{CLR}$ input has a rising signal.

   After a trigger becomes effective, comparators C1 and C2 start operating, and Q_N is turned on. The external capacitor discharges through Q_N. The voltage level at the Rx/Cx node drops. If the Rx/Cx voltage level falls to the internal reference voltage $V_{ref}L$, the output of C1 becomes LOW. The flip-flop is then reset and Q_N turns off. At that moment C1 stops but C2 continues operating.

   After Q_N turns off, the voltage at the Rx/Cx node starts rising at a rate determined by the time constant of external capacitor Cx and resistor Rx.

   Upon triggering, output Q becomes HIGH, following some delay time of the internal F/F and gates. It stays HIGH even if the voltage of Rx/Cx changes from falling to rising. When Rx/Cx reaches the internal reference voltage $V_{ref}H$, the output of C2 becomes LOW, the output Q goes LOW and C2 stops its operation. That means, after triggering, when the voltage level of the Rx/Cx node reaches $V_{ref}H$, the IC returns to its MONOSTABLE state.

   With large values of Cx and Rx, and ignoring the discharge time of the capacitor and internal delays of the IC, the width of the output pulse, t_W (OUT), is as follows:

   t_W (OUT) = 1.0 Cx Rx

3. Reset Operation

   In normal operation, the $\overline{CLR}$ input is held HIGH. If $\overline{CLR}$ is LOW, a trigger has no affect because the Q output is held LOW and the trigger control F/F is reset. Also, Q_p turns on and Cx is charged rapidly to V_{CC}.

   This means if $\overline{CLR}$ is set LOW, the IC goes into a wait state.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to 150°C
Lead Temperature (T_L)	
Soldering, 10 seconds	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{opr})	−40° to +85°C
Input Rise and Fall Time (t_r, t_f) (CLR only)	
V_{CC} = 3.3V ±0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V
External Capacitor - Cx	No Limitation (Note 3) F
External Resistor - Rx	>5 kΩ (Note 3) (V_{CC} = 2.0V)
	>1 kΩ (Note 3) (V_{CC} > 3.0V)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommended operation outside data book specifications.

Note 2: Unused inputs must be used HIGH or LOW. They may not float.

Note 3: The maximum allowable values of Cx and Rx are a function of the leakage of capacitor Cx, the leakage of the device, and leakage due to board layout and surface resistance.

Susceptibility to externally induced noise signals may occur for Rx> 1 MΩ.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40° to 85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44			I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{IN}	Rx/Cx Terminal Off-State Current	5.5			±0.25		±2.50	µA	V_{IN} = V_{CC} or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	
I_{CC}	Active—State (Note 4) Supply Current	3.0		160	250		280	µA	V_{IN} = V_{CC} or GND Rx/Cx = 0.5 V_{CC}	
		4.5		380	500		650			
		5.5		560	750		975			

Note 4: Per Circuit

AC Electrical Characteristics (Note 6)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	3.3 ± 0.3		13.4	20.6	1.0	24.0	ns	C_L = 15 pF
t_{PHL}	(A, B–Q, $\overline{Q}$)			15.9	24.1	1.0	27.5		C_L = 50 pF
		5.0 ± 0.5		8.1	12.0	1.0	14.0	ns	C_L = 15 pF
				9.6	14.0	1.0	16.0		C_L = 50 pF
t_{PLH}	Propagation Delay Time	3.3 ± 0.3		14.5	22.4	1.0	26.0	ns	C_L = 15 pF
t_{PHL}	(CLR Trigger—Q, $\overline{Q}$)			17.0	25.9	1.0	29.5		C_L = 50 pF
		5.0 ± 0.5		8.7	12.9	1.0	15.0	ns	C_L = 15 pF
				10.2	14.9	1.0	17.0		C_L = 50 pF
t_{PLH}	Propagation Delay Time	3.3 ± 0.3		10.3	15.8	1.0	18.5	ns	C_L = 15 pF
t_{PHL}	(CLR—Q, $\overline{Q}$)			12.8	19.3	1.0	22.0		C_L = 50 pF
		5.0 ± 0.5		6.3	9.4	1.0	11.0	ns	C_L = 15 pF
				7.8	11.4	1.0	13.0		C_L = 50 pF
t_{WOUT}	Output Pulse Width	2.0		415				ns	C_X = 28 pF
		3.3 ± 0.3		345					C_L = 50 pF R_X = 6 kΩ
		5.0 ± 0.5		312					
		3.3 ± 0.3		160	240		300	ns	C_L = 50 pF Cx = 28 pF
		5.0 ± 0.5		133	200		240		Rx = 2 kΩ
		3.3 ± 0.3	90	100	110	90	110	µs	C_L = 50 pF Cx = 0.01 µF
		5.0 ± 0.5	90	100	110	90	110		Rx = 10 kΩ
		3.3 ± 0.3	0.9	1.0	1.1	0.9	1.1	ms	C_L = 50 pF Cx = 0.1 µF
		5.0 ± 0.5	0.9	1.0	1.1	0.9	1.1		Rx = 10 kΩ
Δt_{wOUT}	Output Pulse Width Error Between Circuits (In same Package)			±1				%	
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			73				pF	(Note 5)

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

I_{CC} (opr.) = C_{PD}*V_{CC}*f_{IN+} I_{CC}^{1}*Duty/100 + I_{CC}/2 (per Circuit)

I_{CC}^{1}: Active Supply Current

Duty: %

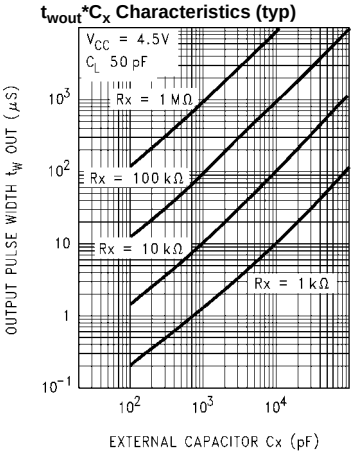
Note 6: Refer to 74VHC221A Timing Chart.

AC Operating Requirement

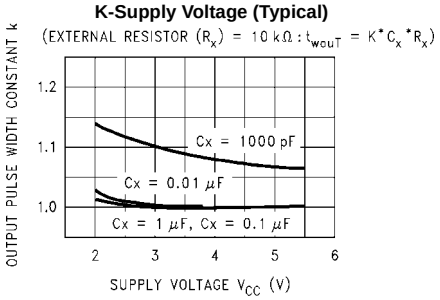
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
t_W(L)	Minimum Trigger	3.3		5.0			5.0	ns
t_W(H)	Pulse Width	5.0		5.0			5.0	
t_W(L)	Minimum Clear	3.3		5.0			5.0	ns
	Pulse Width	5.0		5.0			5.0	

Device Characteristics

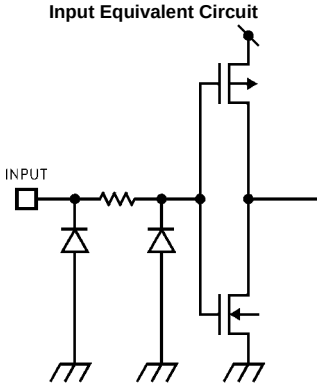
t_{wout}*C_x Characteristics (typ)



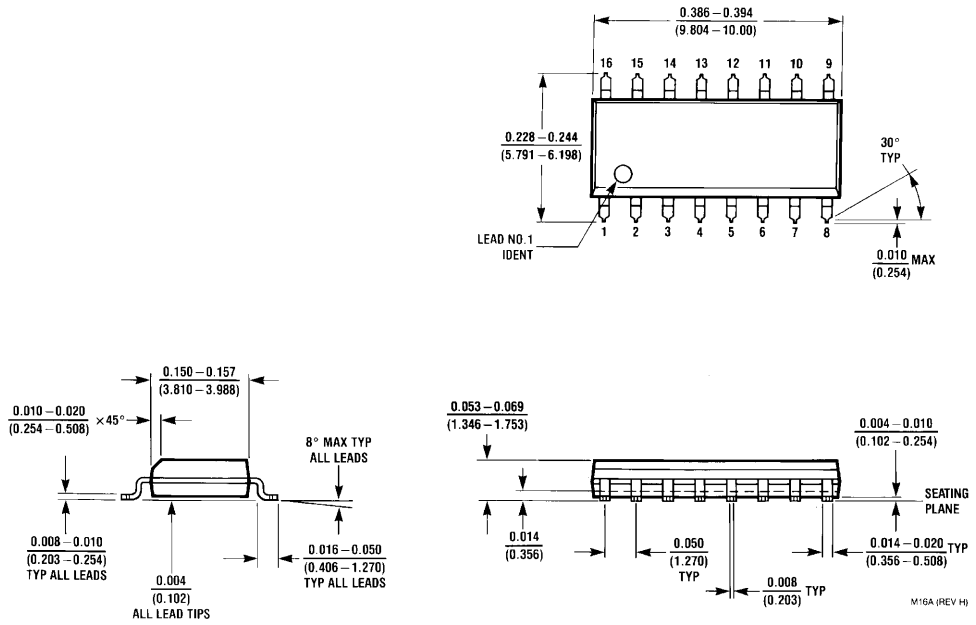
Output Pulse Width Constant K-Supply Voltage (Typical)



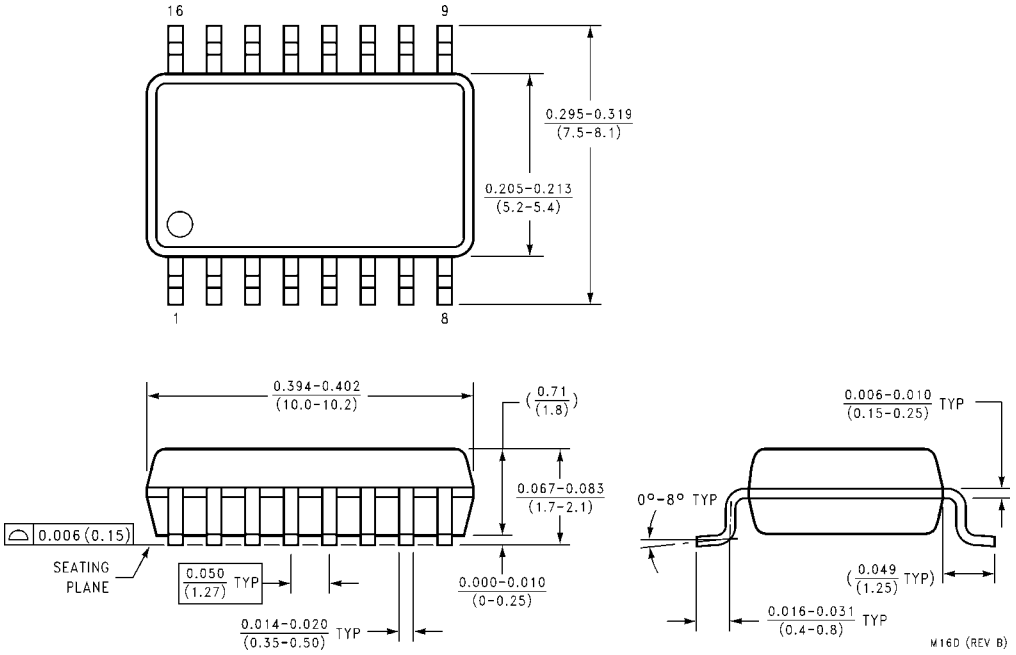
Input Equivalent Circuit



Physical Dimensions inches (millimeters) unless otherwise noted

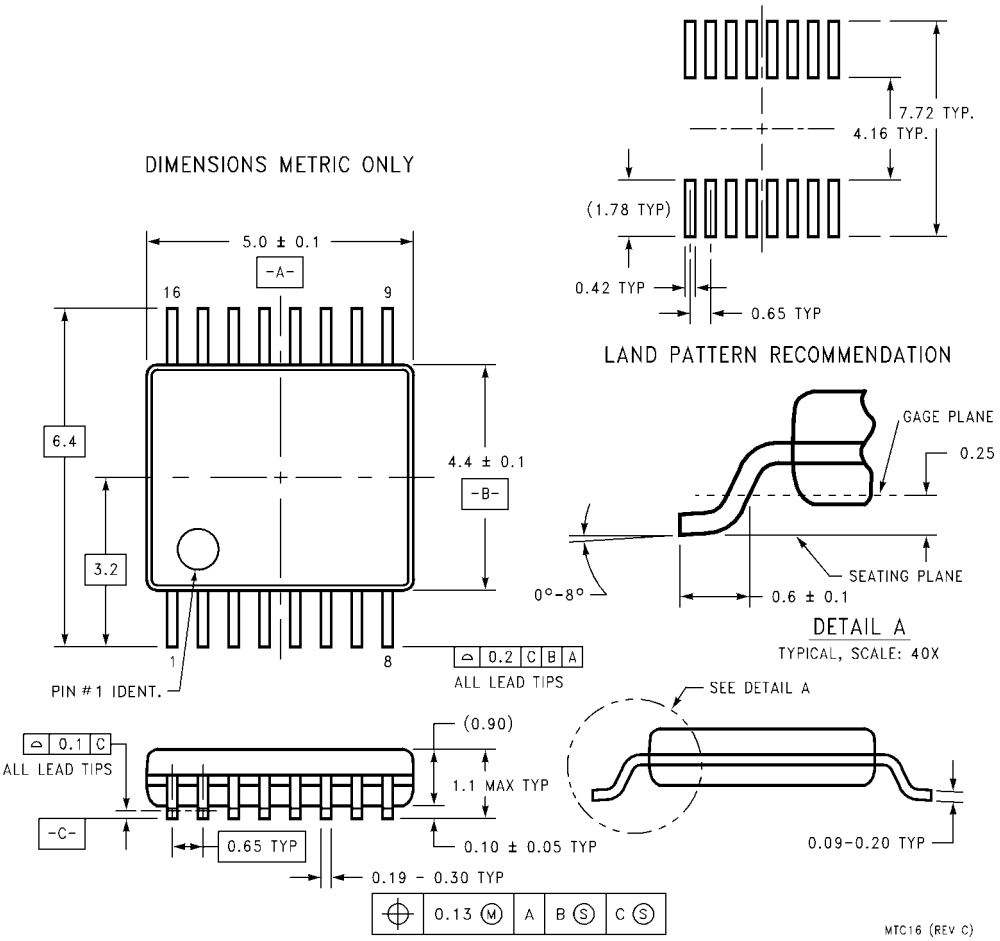


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



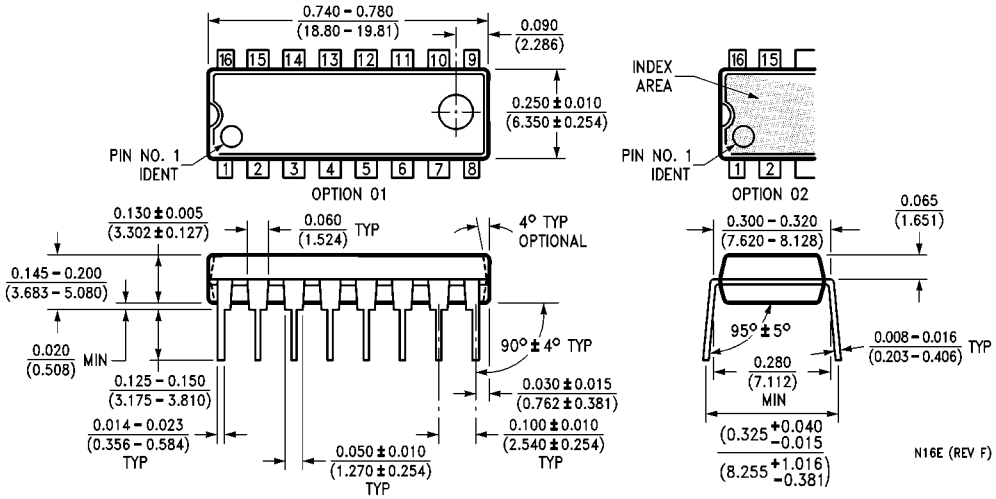
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

October 1992
Revised March 1999

74VHC240
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHC240 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC240 is an inverting 3-STATE buffer having two active-LOW output enables. This device is designed to drive buslines or buffer memory address registers.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

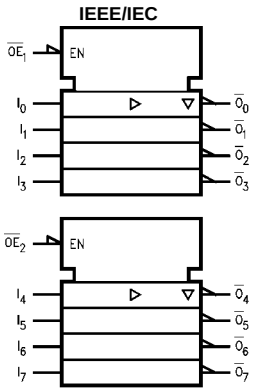
- High Speed: t_{PD} = 3.6ns (typ) at T_A = 25°C
- Low power dissipation: I_{CC} = 4 μA (max) @ T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.9V (max)
- Pin and function compatible with 74HC240

Ordering Code:

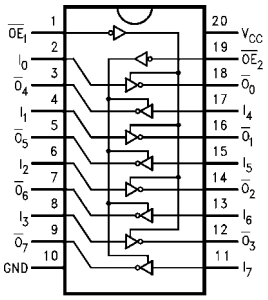
Order Number	Package Number	Package Description
74VHC240M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC240N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs 3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables.Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

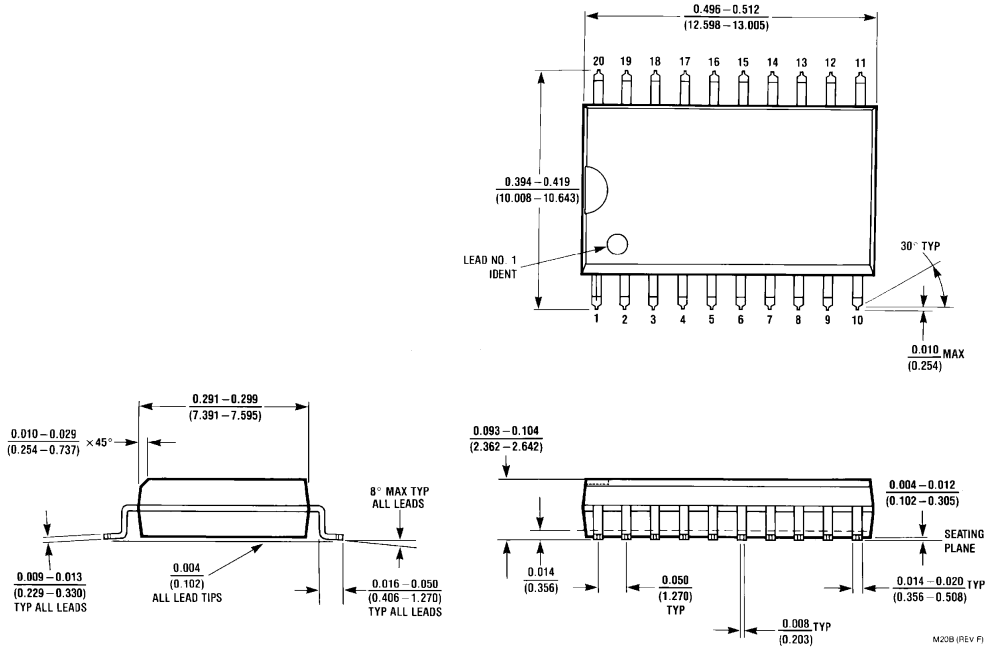
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation	3.3 ± 0.3		5.3	7.5	1.0	9.0	ns		$C_L = 15$ pF
t_{PHL}	Delay Time			7.8	11.0	1.0	12.5			$C_L = 50$ pF
		5.0 ± 0.5		3.6	5.5	1.0	6.5	ns		$C_L = 15$ pF
				5.1	7.5	1.0	8.5			$C_L = 50$ pF
t_{PZL}	3-STATE	3.3 ± 0.3		6.6	10.6	1.0	12.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Output			9.1	14.1	1.0	16.0			$C_L = 50$ pF
	Enable Time	5.0 ± 0.5		4.7	7.3	1.0	8.5	ns		$C_L = 15$ pF
				6.2	9.3	1.0	10.5			$C_L = 50$ pF
t_{PLZ}	3-STATE	3.3 ± 0.3		10.3	14.0	1.0	16.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Output Disable Time	5.0 ± 0.5	6.7		9.2	1.0	10.5			$C_L = 50$ pF
t_{OSLH}	Output to	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	$C_L = 50$ pF
t_{OSHL}	Output Skew	5.0 ± 0.5			1.0		1.0			$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			17				pF	(Note 5)	

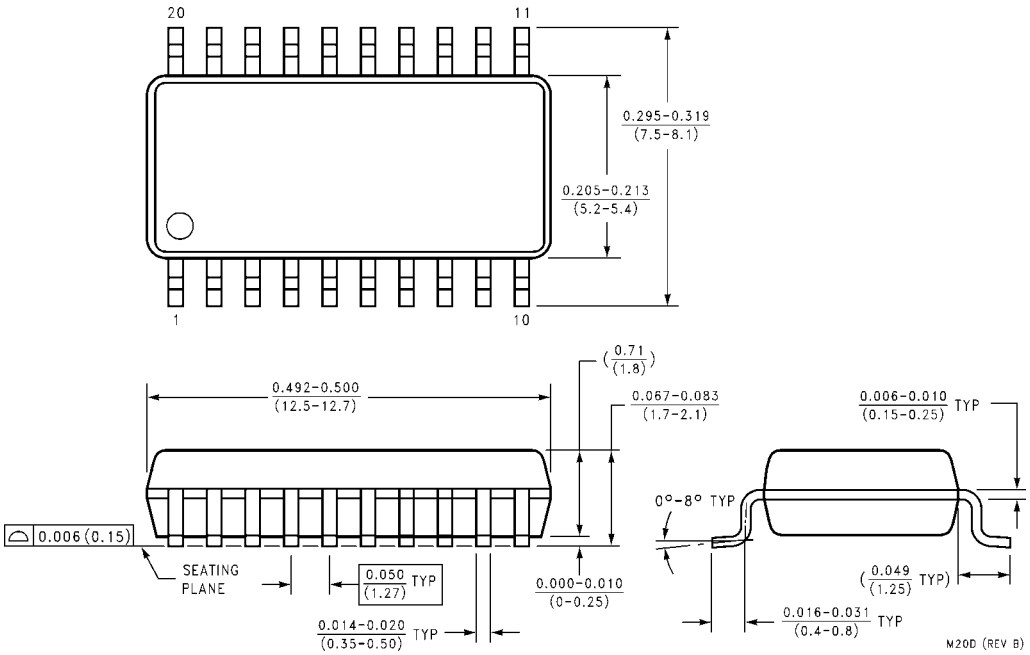
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

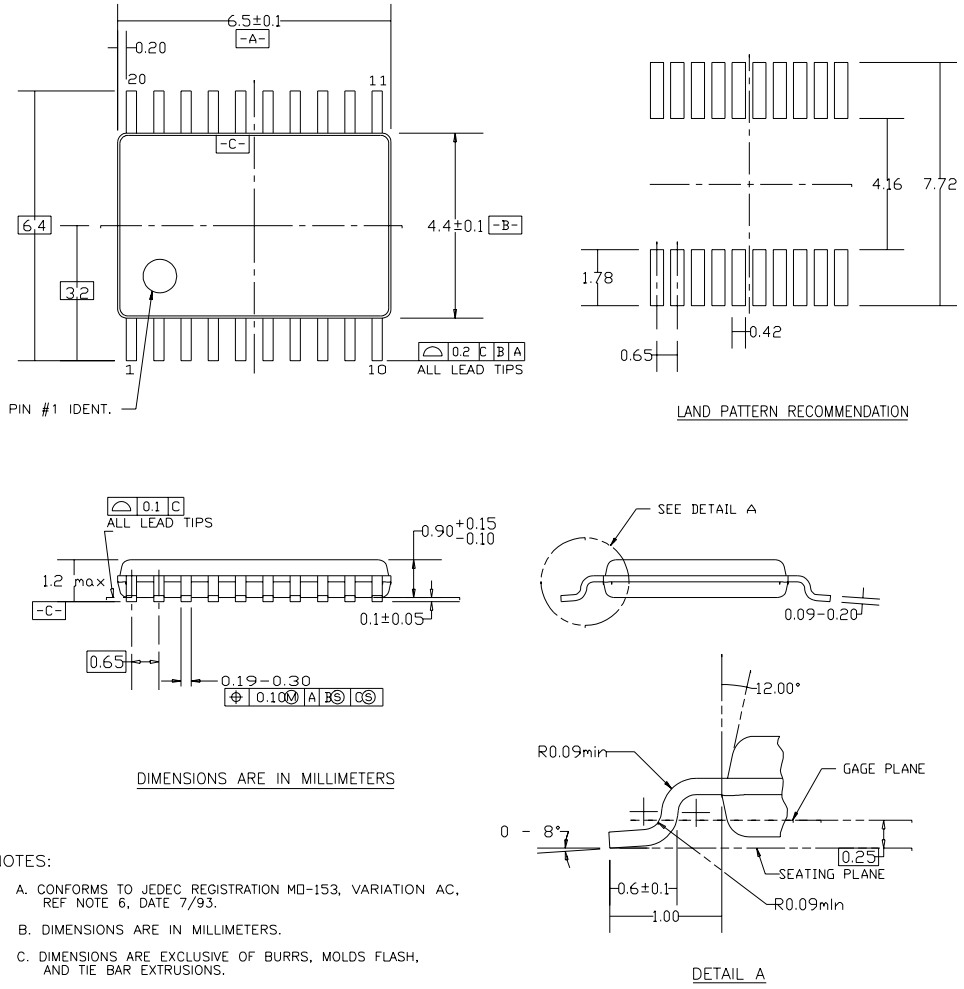


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

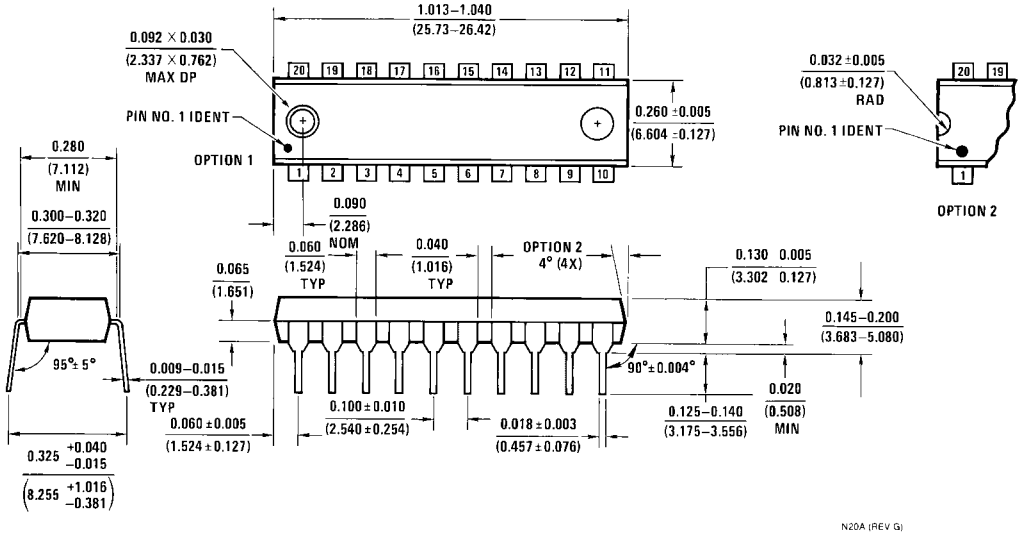
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised April 1999

74VHC244
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHC244 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC244 is a non-inverting 3-STATE buffer having two active-LOW output enables. These devices are designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

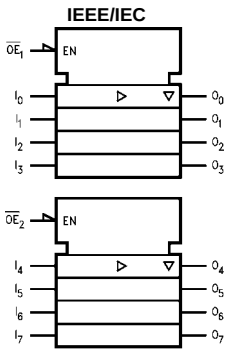
- High Speed: t_{PD} = 3.9ns (typ) at V_{CC} = 5V
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.6V (typ)
- Low power dissipation: I_{CC} = 4 μA (max) @ T_A = 25°C
- Pin and function compatible with 74HC244

Ordering Code:

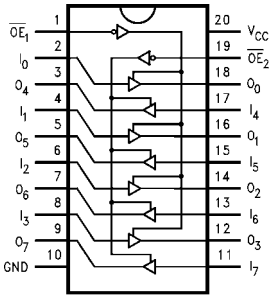
Order Number	Package Number	Package Description
74VHC244M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC244N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
I = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.5			1.5		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.5		0.5	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Output Voltage	3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Output Voltage	3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum HIGH Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

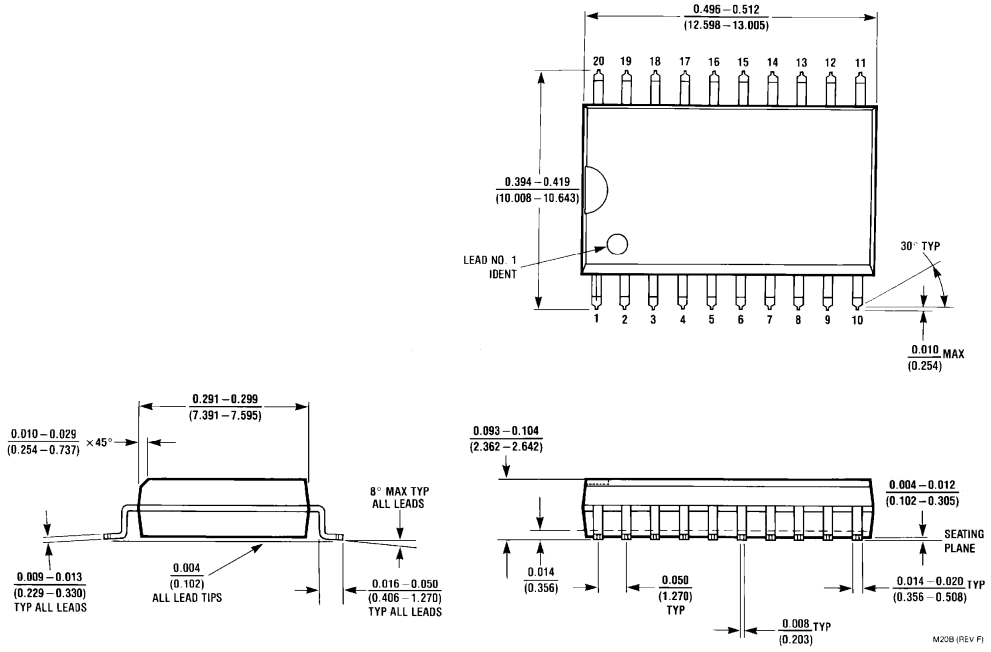
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		5.8	8.4	1.0	10.0	ns		C_L = 15 pF
t_{PHL}	Time			8.3	11.9	1.0	13.5			C_L = 50 pF
		5.0 ± 0.5		3.9	5.5	1.0	6.5	ns		C_L = 15 pF
				5.4	7.5	1.0	8.5			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		6.6	10.6	1.0	12.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			9.1	14.1	1.0	16.0			C_L = 50 pF
		5.0 ± 0.5		4.7	7.3	1.0	8.5	ns		C_L = 15 pF
				6.2	9.3	1.0	10.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		10.3	14.0	1.0	16.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ± 0.5		6.7	9.2	1.0	10.5			C_L = 50 pF
t_{OSLH}	Output to Output	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C_L = 50 pF
t_{OSHL}	Skew	5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 5)	

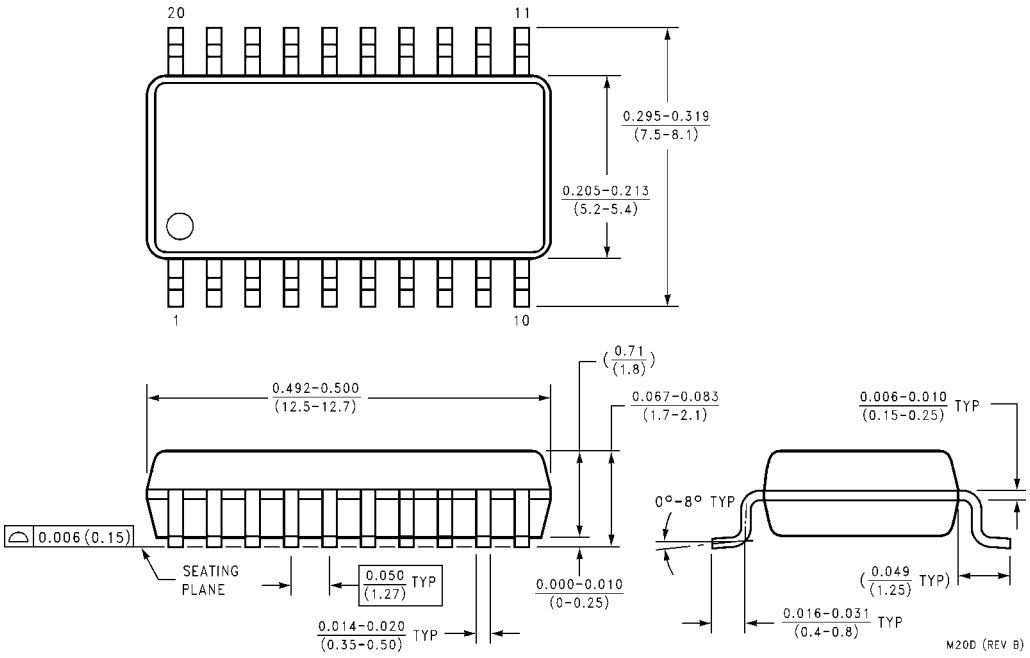
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

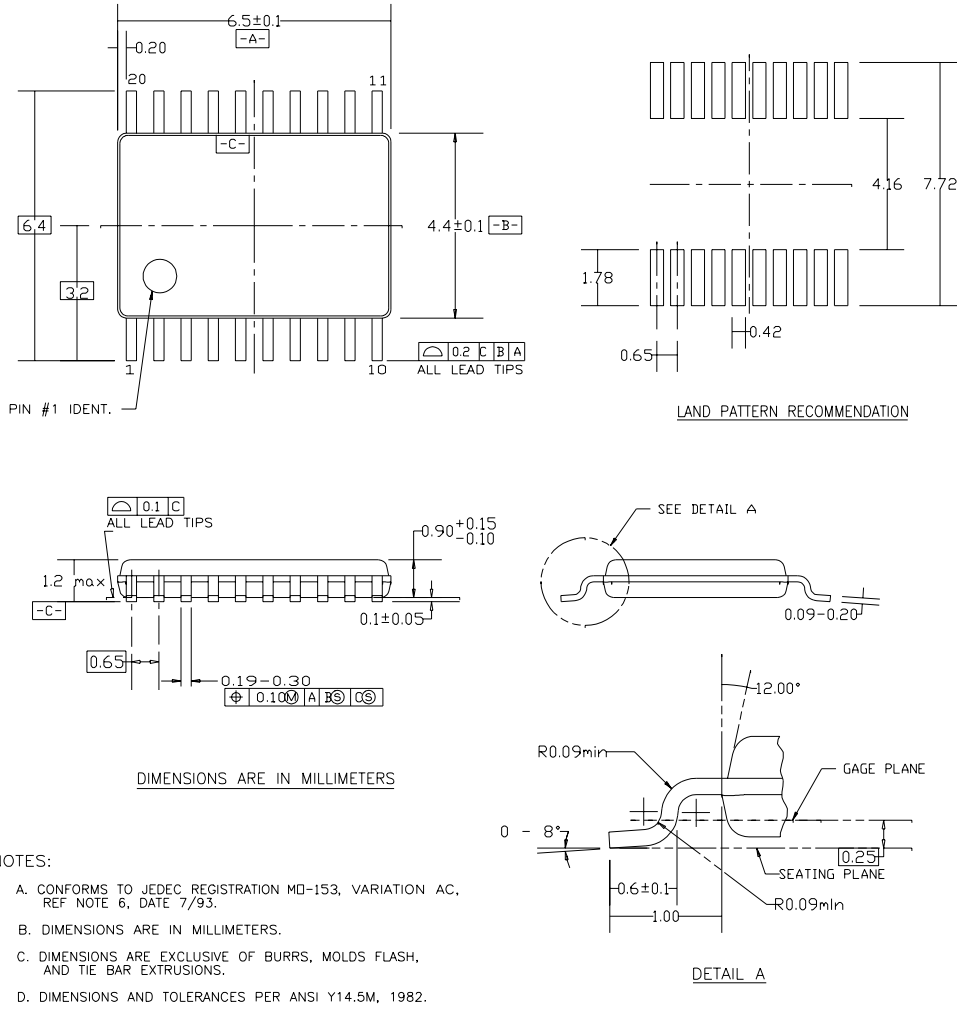


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

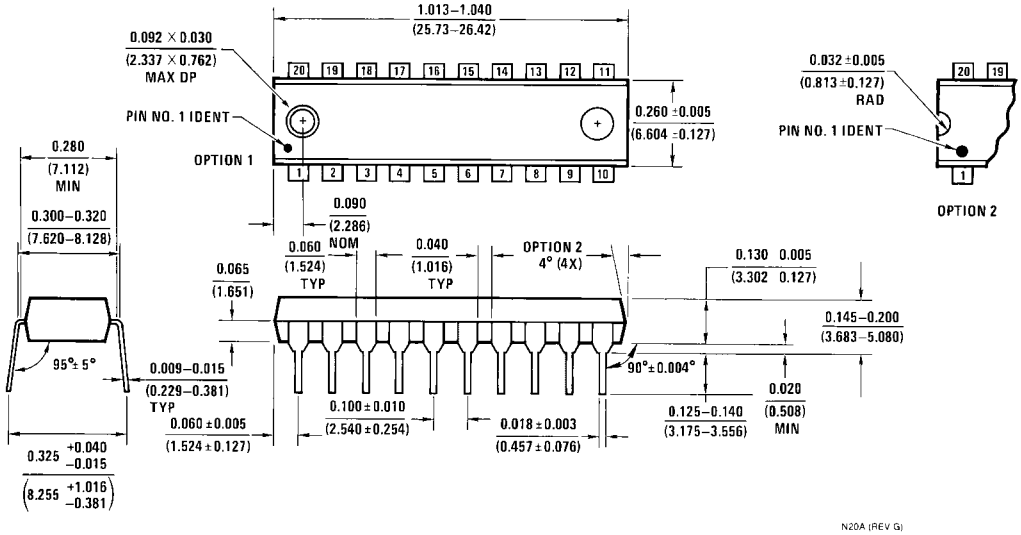
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

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November 1992
Revised March 1999

74VHC245
Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The VHC245 is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC245 is intended for bidirectional asynchronous communication between data busses. The direction of data transmission is determined by the level of the T/$\overline{R}$ input. The enable input can be used to disable the device so that the busses are effectively isolated. All inputs are equipped with protection circuits against static discharge.

Features

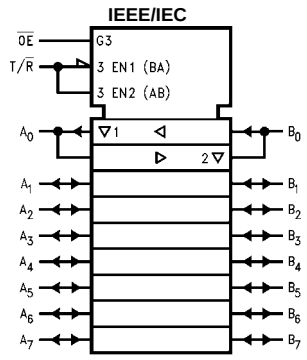
- High Speed: t_{PD} = 4.0 ns (typ) at V_{CC} = 5V
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power Down Protection is provided on all inputs
- Low Noise: V_{OLP} = 0.9V (typ)
- Low Power Dissipation:
  I_{CC} = 4 μA (Max) @ T_A = 25°C
- Pin and Function Compatible with 74HC245

Ordering Code:

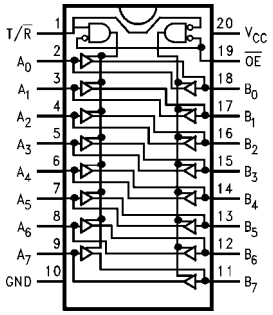
Order Number	Package Number	Package Description
74VHC245M	M20B	20-Lead Small Outline Integrated Package (SOIC), JEDEC MS-013, 0.300" Wide
74VHC245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC245N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial
Any unused bus terminals during HIGH-Z State must be held HIGH or LOW.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN}) (T/$\overline{R}$, $\overline{OE}$)	−0.5V to 7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK}) (T/$\overline{R}$, $\overline{OE}$)	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 5.5V
Input Voltage (V_{IN})(T/$\overline{R}$, $\overline{OE}$)	0V to 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{CC} or GND; V_{OUT} = V_{CC} or GND; V_{IN} $\overline{OE}$ = V_{IH} or V_{IL}	
I_{IN} (T/$\overline{R}$, $\overline{OE}$)	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	$C_L = 50$ pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.9	−1.2	V	$C_L = 50$ pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	$C_L = 50$ pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	$C_L = 50$ pF

Note 3: Parameter guaranteed by design.

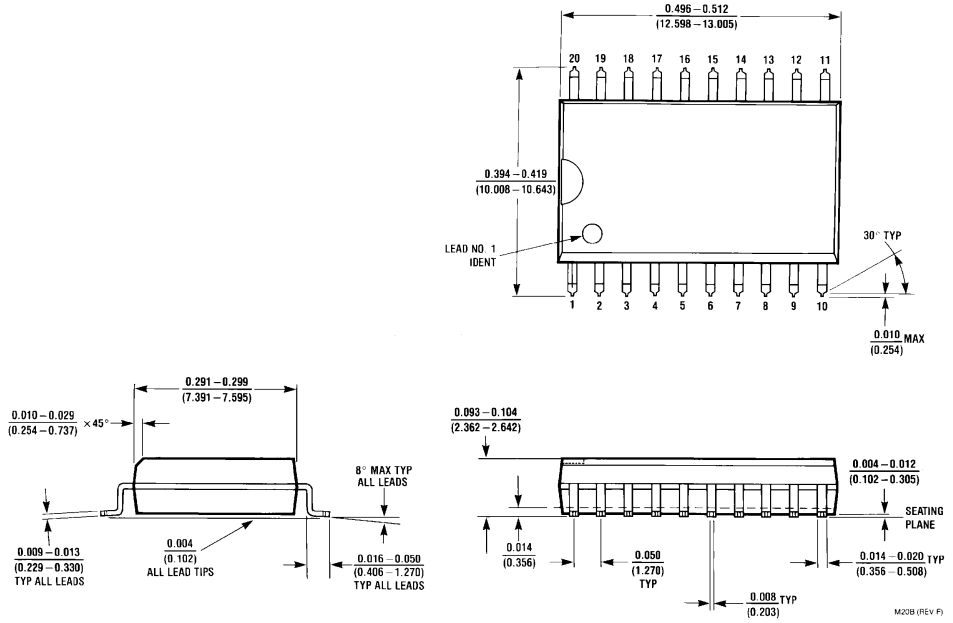
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH} t_{PHL}	Propagation Delay Time	3.3 ± 0.3		5.8	8.4	1.0	10.0	ns		$C_L = 15$ pF
				8.3	11.9	1.0	13.5			$C_L = 50$ pF
		5.0 ± 0.5		4.0	5.5	1.0	6.5	ns		$C_L = 15$ pF
				5.5	7.5	1.0	8.5			$C_L = 50$ pF
t_{PZL} t_{PZH}	3-STATE Output Enable Time	3.3 ± 0.3		8.5	13.2	1.0	15.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
				11.0	16.7	1.0	19.0			$C_L = 50$ pF
		5.0 ± 0.5		5.8	8.5	1.0	10.0	ns		$C_L = 15$ pF
				7.3	10.6	1.0	12.0			$C_L = 50$ pF
t_{PLZ} t_{PHZ}	3-STATE Output Disable Time	3.3 ± 0.3		11.5	15.8	1.0	18.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
		5.0 ± 0.5		7.0	9.7	1.0	11.0			$C_L = 50$ pF
t_{OSLH} t_{OSHL}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	$C_L = 50$ pF
		5.0 ± 0.5			1.0		1.0			$C_L = 50$ pF
C_{IN} ($T/\overline{R}$, $\overline{OE}$)	Input Capacitance			4	10		10	pF	V_{CC} = Open	
$C_{I/O}$	Output Capacitance			8				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			21				pF	(Note 5)	

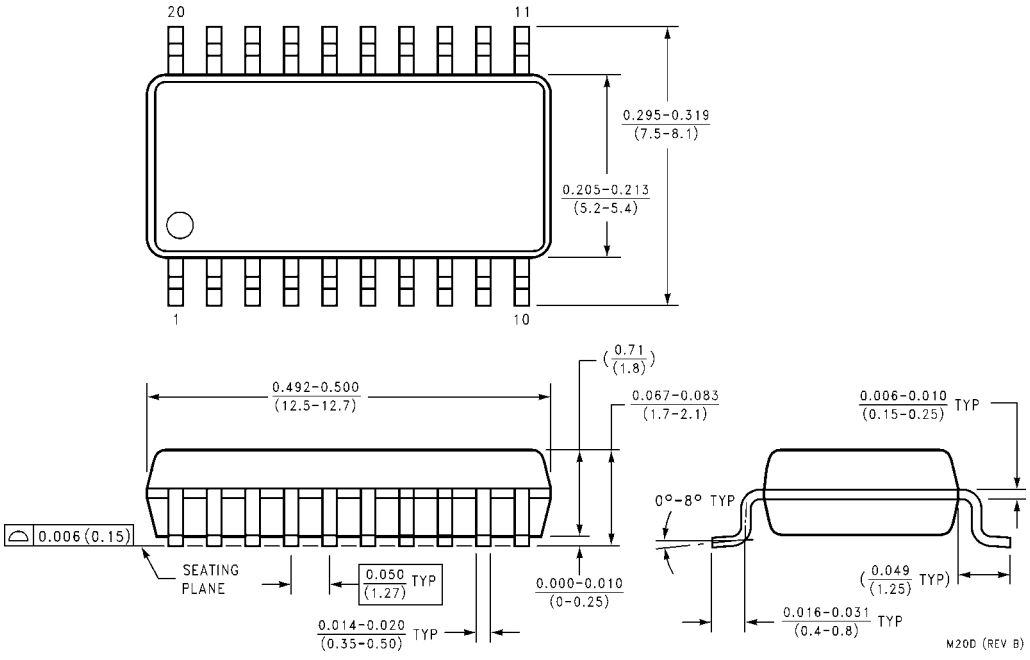
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per Bit).

Physical Dimensions inches (millimeters) unless otherwise noted

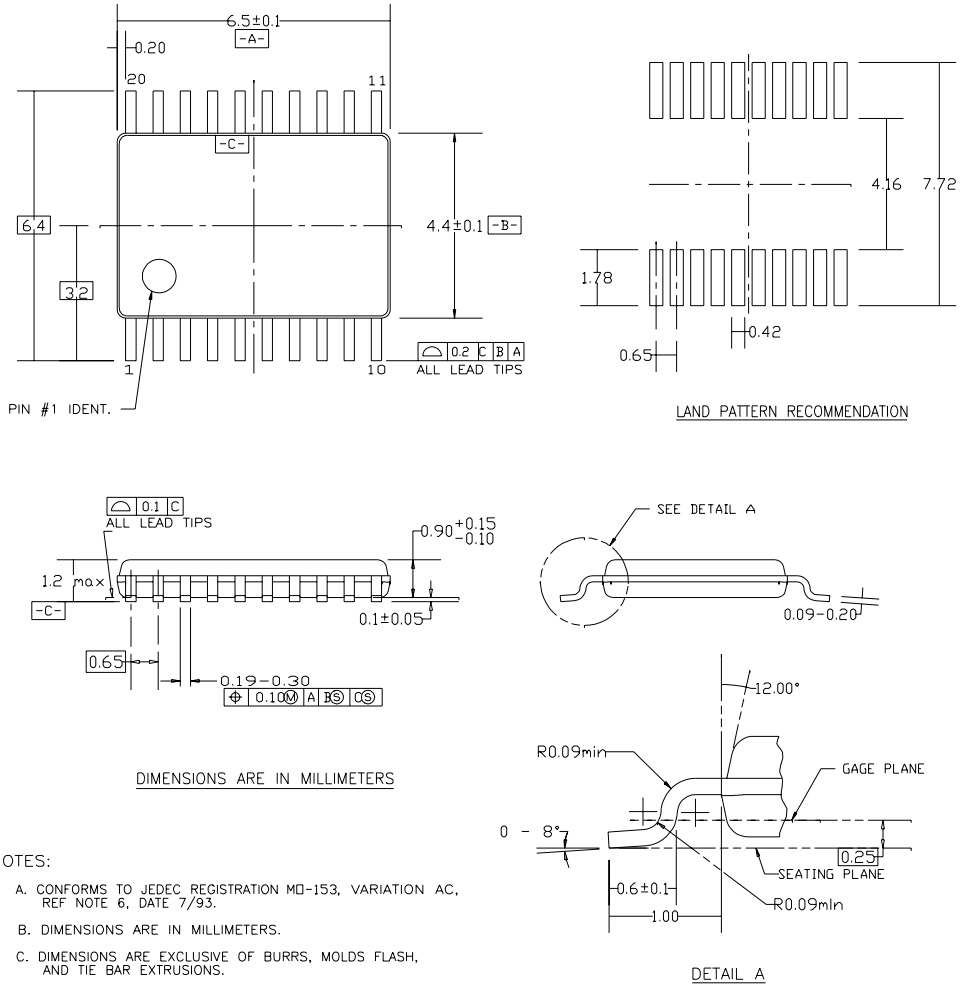


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

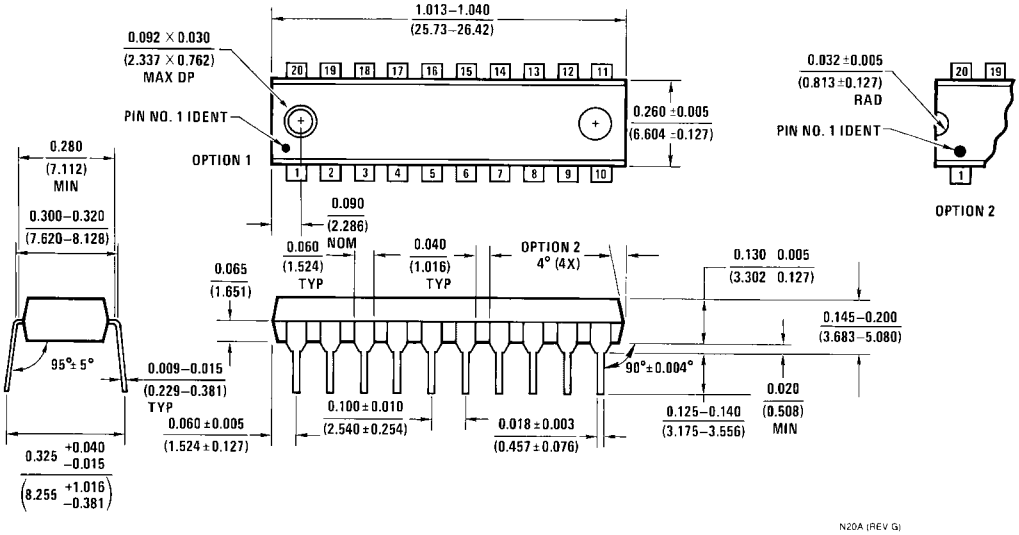
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

National Semiconductor

PRELIMINARY
October 1995

74VHC257
Quad 2-Input Multiplexer with TRI-STATE® Outputs

General Description

The VHC257 is an advanced high speed CMOS Quad 2-Channel Multiplexer featuring TRI-STATE outputs. It is fabricated with silicon gate CMOS technology and achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of four 2-input digital multiplexers with common select and enable ($\overline{OE}$) inputs.

When the $\overline{OE}$ input is held to a logic HIGH, the outputs are switched to a high impedance state, allowing the outputs to interface directly with bus-oriented systems.

The SELECT decoding determines whether the I_{0x} or I_{1x} inputs get routed to their corresponding outputs.

An Input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

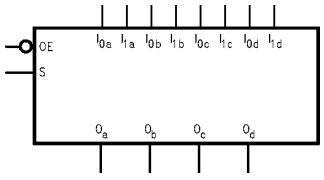
Features

- High speed
- Low power dissipation:
  I_{CC} = 4 μA (max.) at T_A = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min.)
- All inputs are equipped with a power down protection function
- Balanced propagation delays: $t_{PLH} \cong t_{PHL}$
- Wide operating voltage range: V_{CC} (opr) = 2V ~ 5.5V
- Low noise: V_{OLP} = 0.8V (max.)
- Pin and function compatible with 74HC257

Commercial	Package Number	Package Description
74VHC257M	M16A	16-Lead Molded JEDEC SOIC
74VHC257SJ	M16D	16-Lead Molded EIAJ SOIC
74VHC257MTC	MTC16	16-Lead Molded JEDEC Type 1 TSSOP
74VHC257N	N16E	16-Lead Molded DIP

Note: Surface mount packages are also available on Tapeand Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



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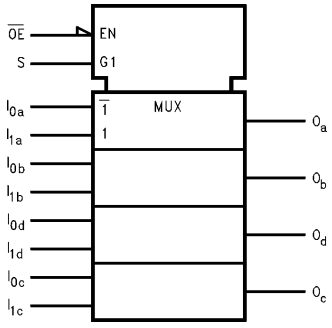

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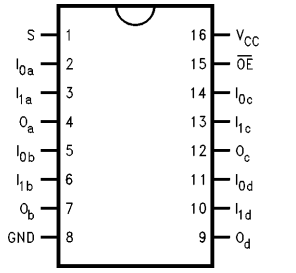
Pin Names	Description
I_{0a}–I_{0d}	Source 0 Data Inputs
I_{1a}–I_{1d}	Source 1 Data Inputs
$\overline{OE}$	Output Enable
S	Select Input
O_a–O_d	Outputs

Connection Diagram

Pin Assignment for DIP, TSSOP, and SOIC



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TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Functional Description

The 'VHC257 is a quad 2-input multiplexer with TRI-STATE outputs. It selects four bits of data from two sources under the control of a Common Data Select Input. When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The device is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$O_a = \overline{OE} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$

$O_b = \overline{OE} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$

$O_c = \overline{OE} \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S})$

$O_d = \overline{OE} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$

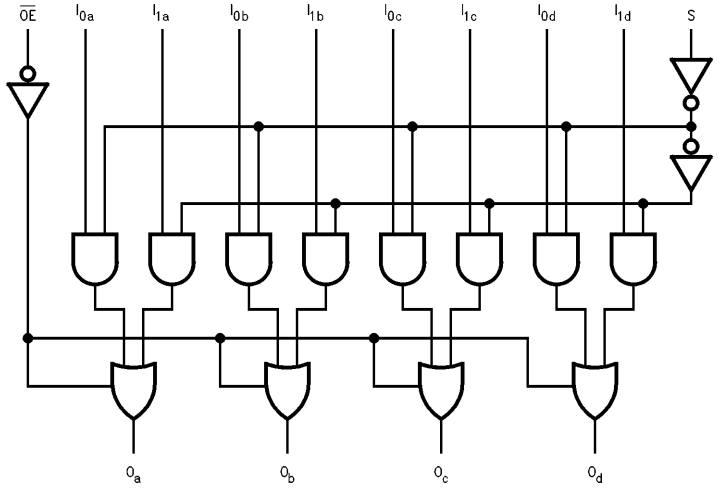
When the Output Enabler ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure the Output Enable signals to TRI-STATE devices whose outputs are tied together are designed so there is no overlap.

Truth Table

Output Enable	Select Input	Data Inputs		Outputs
$\overline{OE}$	S	I_0	I_1	O
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



TL/F/11659–3

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C

Note 1: *Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation outside databook specifications.*

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

DC Characteristics for 'VHC Family Devices (Preliminary)

Symbol	Parameter	V_{CC} (V)	74VHC T_A = 25°C			74VHC T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0 3.0–5.5	1.50 0.7 V_{CC}			1.50 0.7 V_{CC}		V		
V_{IL}	Low Level Input Voltage	2.0 3.0–5.5			0.50 0.3 V_{CC}		0.50 0.3 V_{CC}	V		
V_{OH}	High Level Output Voltage	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0 4.5	2.58 3.94			2.48 3.80		V		I_{OH} = −4 mA I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0 4.5			0.36 0.36		0.44 0.44	V		I_{OL} = 4 mA I_{OL} = 8 mA
I_{OZ}	TRI-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

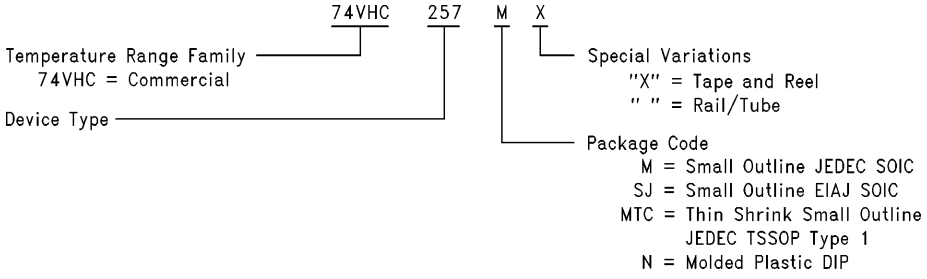
AC Electrical Characteristics (Preliminary)

Symbol	Parameter	V_{CC} (V)	74VHC $T_A = 25°C$			74VHC $T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}, t_{PHL}	Propagation Delay I_n to O_n	3.3 ±0.3		6.2	9.7	1.0	11.5	ns		$C_L = 15$ pF
				8.7	13.2	1.0	15.0			$C_L = 50$ pF
		5.0 ±0.5		4.1	6.4	1.0	7.5	ns		$C_L = 15$ pF
				5.6	8.4	1.0	9.5			$C_L = 50$ pF
t_{PLH}, t_{PHL}	Propagation Delay S to O_n	3.3 ±0.3		8.4	13.2	1.0	15.5	ns		$C_L = 15$ pF
				10.9	16.7	1.0	19.0			$C_L = 50$ pF
		5.0 ±0.5		5.3	8.1	1.0	9.5	ns		$C_L = 15$ pF
				6.8	10.1	1.0	11.5			$C_L = 50$ pF
t_{PZL}, t_{PZH}	TRI-STATE Output Enable Time	3.3 ±0.3		8.7	13.6	1.0	16.0	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
				11.2	17.1	1.0	19.5			$C_L = 50$ pF
		5.0 ±0.5		5.6	8.6	1.0	10.0	ns		$C_L = 15$ pF
				7.1	10.6	1.0	12.0			$C_L = 50$ pF
t_{PLZ}, t_{PHZ}	TRI-STATE Output Disable Time	3.3 ±0.3						ns	$R_L = 1$ kΩ	$C_L = 50$ pF
		5.0 ±0.5						ns		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance							pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			20				pF	(Note 1)	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

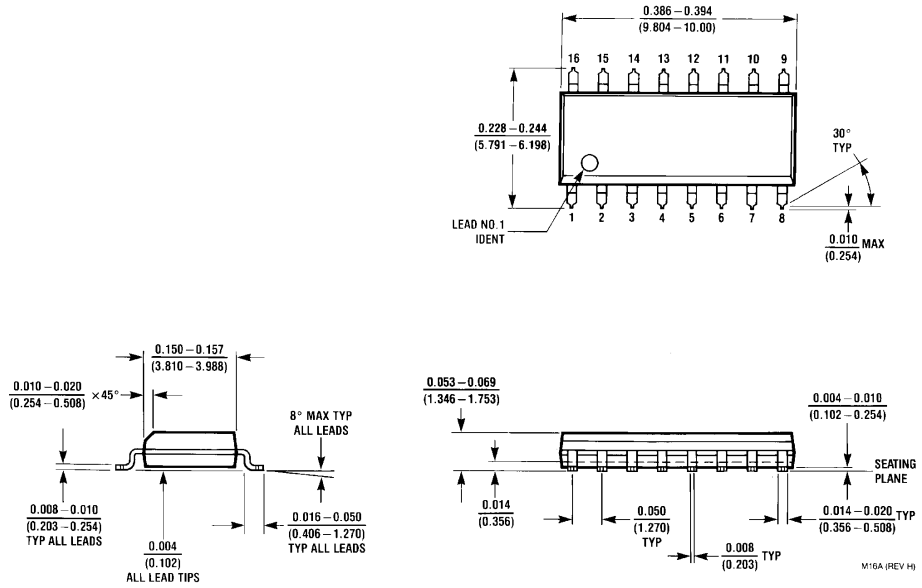
Ordering Information

The device number is used to form part of a simplified purchasing code, where the package type and temperature range are defined as follows:



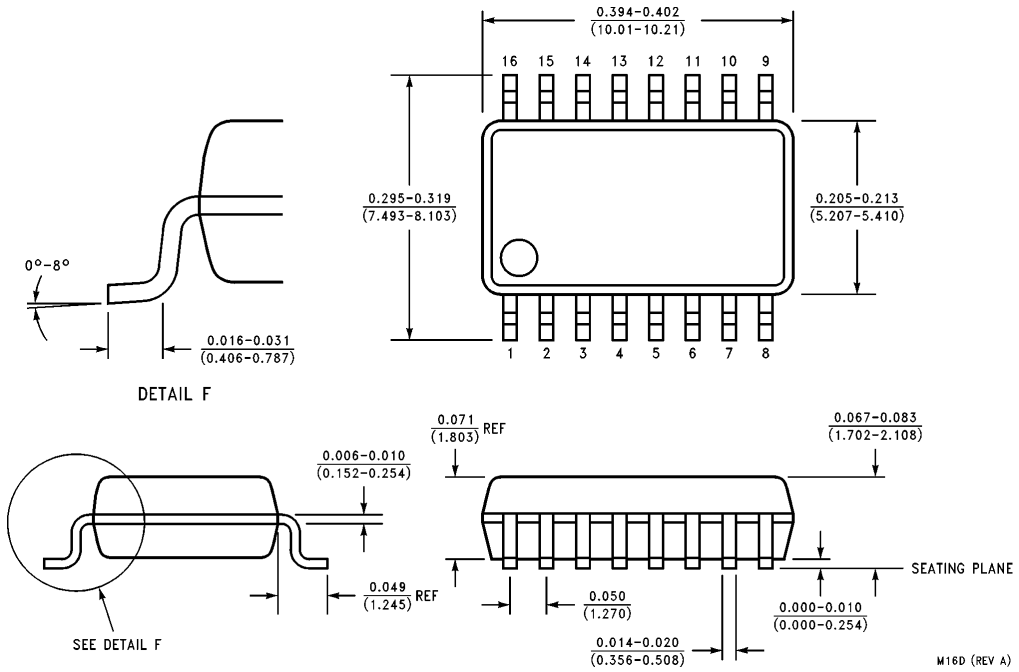
TL/F/11659–4

Physical Dimensions inches (millimeters)



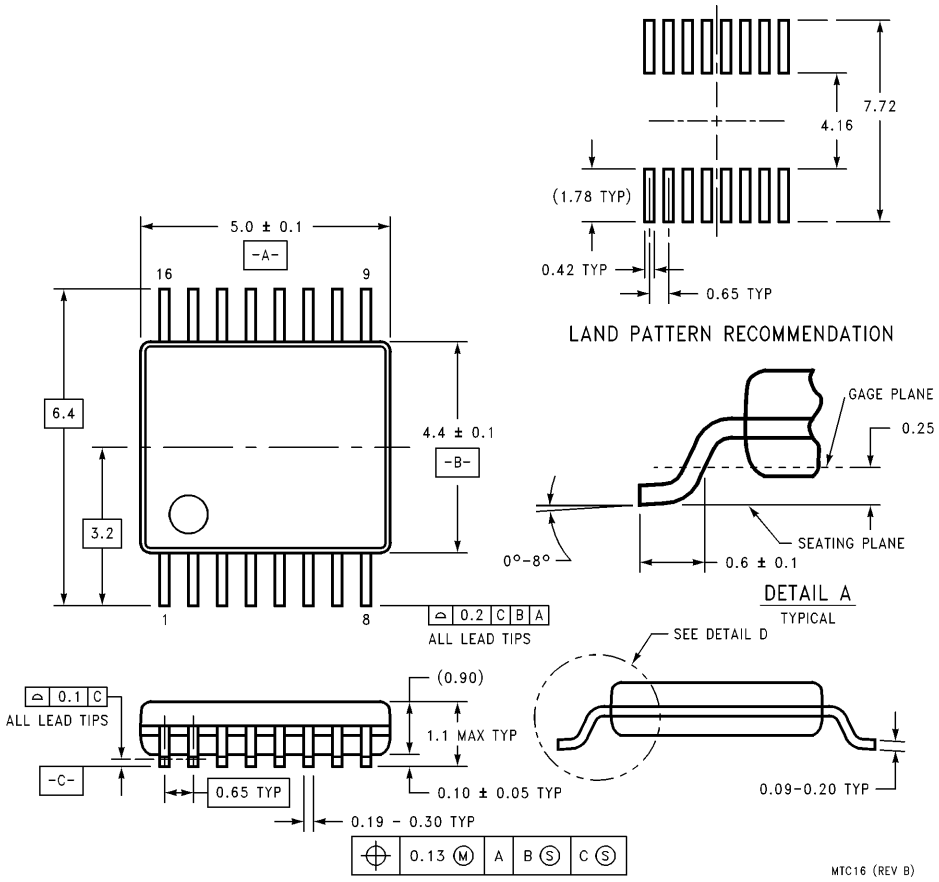
16-Lead Small Outline Integrated Circuit—JEDEC (M)
Order Number 74VHC257M
NS Package Number M16A

Physical Dimensions inches (millimeters) (Continued)



16-Lead Small Outline Package-EIAJ (SJ)
Order Number 74VHC257SJ
NS Package Number M16D

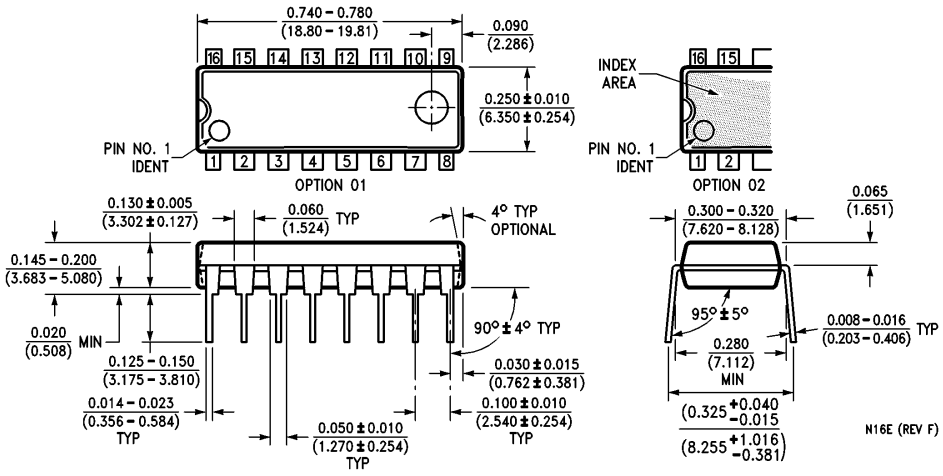
Physical Dimensions (millimeters) (Continued)



All dimensions are in millimeters.

16-Lead Molded Thin Shrink Small Outline Package; JEDEC
Order Number 74VHC257MTC
NS Package Number MTC16

Physical Dimensions inches (millimeters) (Continued)



16-Lead (0.300″ Wide) Molded Dual-In-Line Package
Order Number 74VHC257N
NS Package Number N16E

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FAIRCHILD SEMICONDUCTOR™

July 1994
Revised April 1999

74VHC27
Triple 3-Input NOR Gate

General Description

The VHC27 is an advanced high speed CMOS 3-Input NOR Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

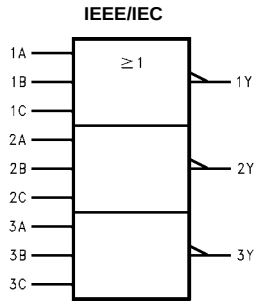
- High speed: t_{PD} = 4.1 ns (typ) at T_A = 25°C
- Low power dissipation: I_{CC} = 2 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC27

Ordering Code:

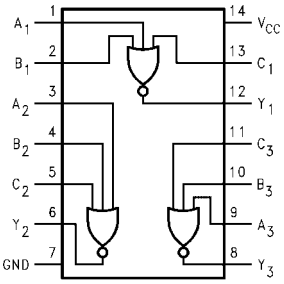
Order Number	Package Number	Package Description
74VHC27M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHC27SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC27MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC27N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n, C_n	Inputs
Y_n	Outputs

Truth Table

A	B	C	Y
H	X	X	L
X	H	X	L
X	X	H	L
L	L	L	H

X = Don't Care

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

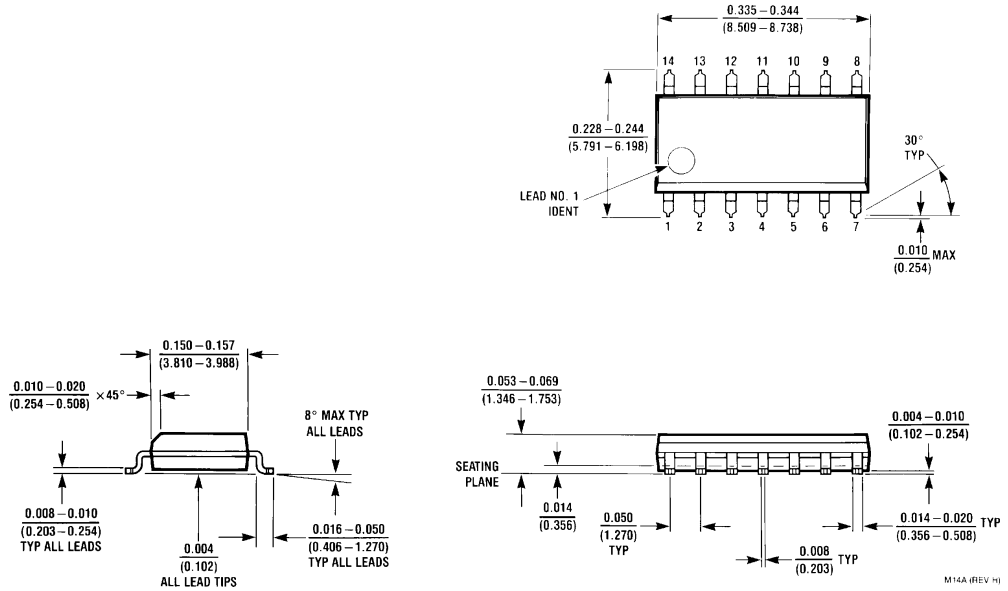
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

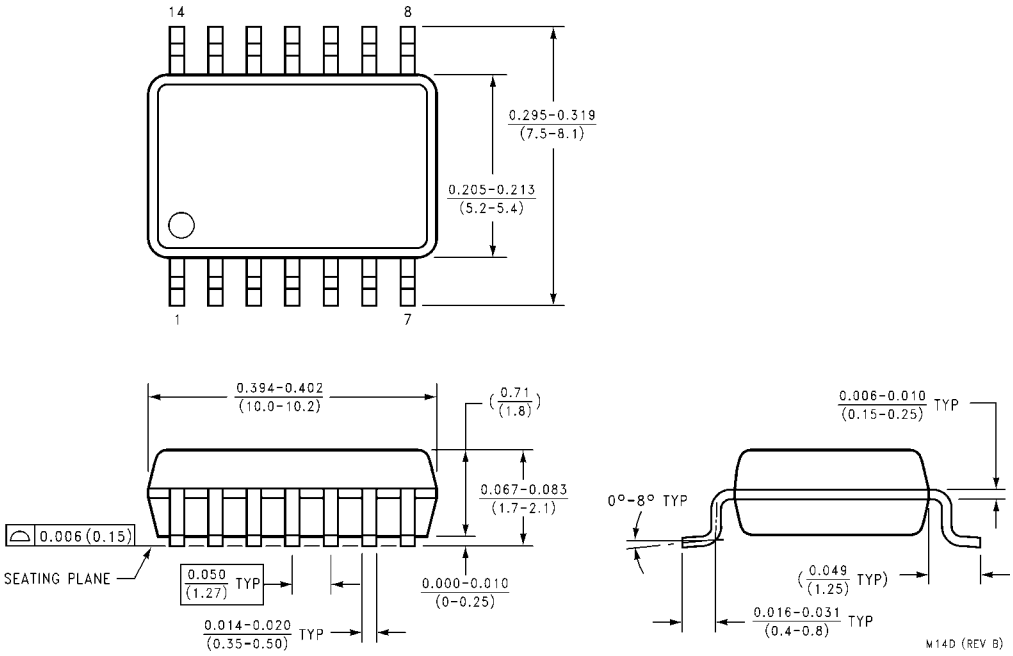
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL}	Propagation Delay	3.3 ± 0.3		6.2	8.8	1.0	10.5	ns	$C_L = 15$ pF
t_{PLH}				8.7	12.3	1.0	14.0		$C_L = 50$ pF
		5.0 ± 0.5		4.1	5.9	1.0	7.0	ns	$C_L = 15$ pF
				5.6	7.9	1.0	9.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			20				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/3$ (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

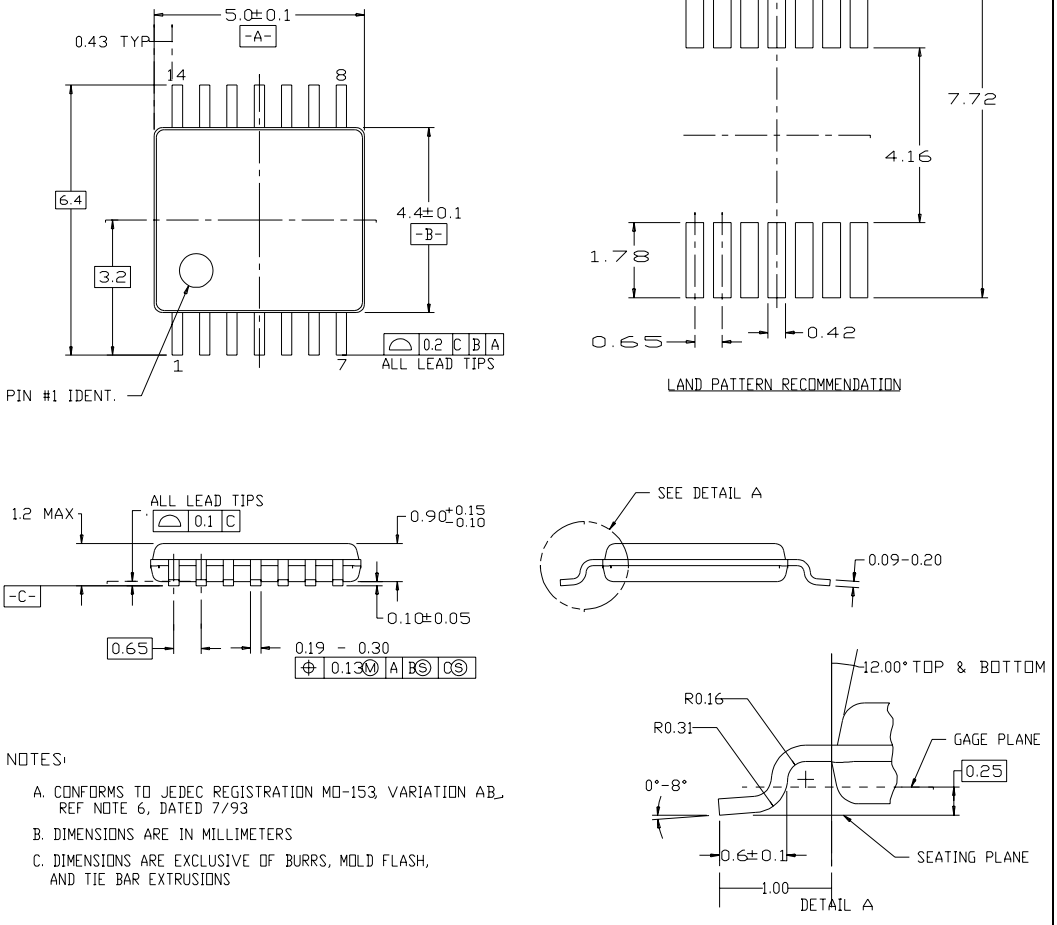


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

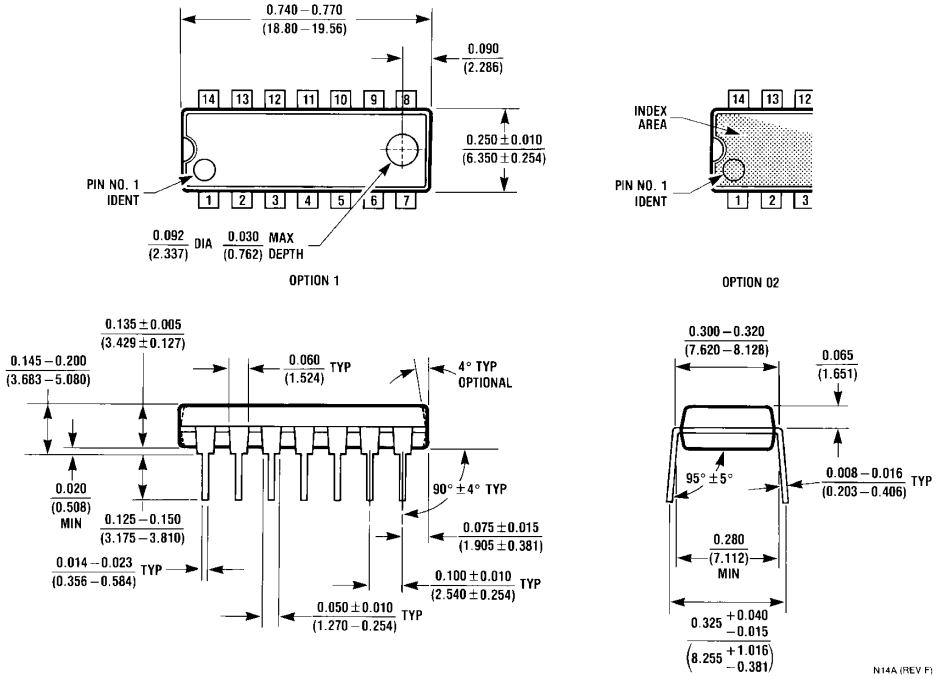
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1994
Revised April 1999

74VHC273
Octal D-Type Flip-Flop

General Description

The VHC273 is an advanced high speed CMOS Octal D-type flip-flop fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The register has a common buffered Clock (CP) which is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output. The Master Reset ($\overline{MR}$) input will clear all flip-flops simultaneously. All outputs will be forced LOW independently of Clock or Data inputs by a LOW voltage level on the $\overline{MR}$ input.

An input protection circuit insures that 0V to 7V can be applied to the inputs pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

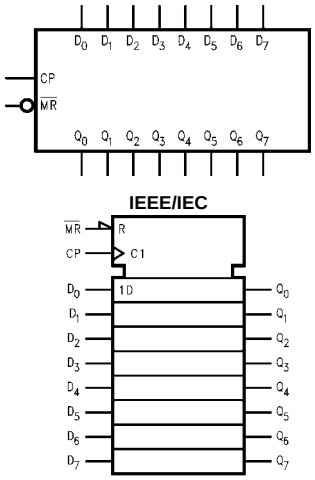
- High Speed: f_{MAX}= 165 MHz (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.9V (max)
- Pin and function compatible with 74HC273

Ordering Code:

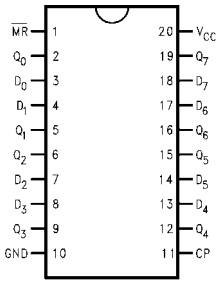
Order Number	Package Number	Package Description
74VHC273M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHC273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC273N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

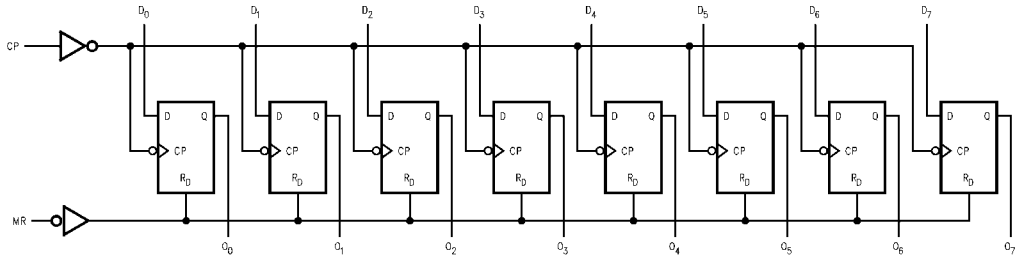
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{MR}$	Master Reset
CP	Clock Pulse Input
Q_0–Q_7	Data Outputs

Function Table

Operating Mode	Inputs			Outputs
	$\overline{MR}$	CP	D_n	Q_n
Reset (Clear)	L	X	X	L
Load '1'	H	⌐	H	H
Load '0'	H	⌐	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	75	120		65		MHz		C_L = 15 pF
			50	75		45				C_L = 50 pF
		5.0 ± 0.5	120	165		100		MHz		C_L = 15 pF
			80	110		70				C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time (CK - Q)	3.3 ± 0.3		8.7	13.6	1.0	16.0	ns		C_L = 15 pF
				11.2	17.1	1.0	19.5			C_L = 50 pF
		5.0 ± 0.5		5.8	9.0	1.0	10.5	ns		C_L = 15 pF
				7.3	11.0	1.0	12.5			C_L = 50 pF
t_{PHL}	Propagation Delay Time ($\overline{MR}$ - Q)	3.3 ± 0.3		8.9	13.6	1.0	16.0	ns		C_L = 15 pF
				11.4	17.1	1.0	19.5			C_L = 50 pF
		5.0 ± 0.5		5.2	8.5	1.0	10.0	ns		C_L = 15 pF
				6.7	10.5	1.0	12.0			C_L = 50 pF
t_{OSLH}	Output to	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C_L = 50 pF
t_{OSHL}	Output Skew	5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{PD}	Power Dissipation Capacitance			31				pF	(Note 5)	

Note 4: Parameter guaranteed by design $t_{OSLH} = |t_{PLH}max - t_{PLH}min|$; $t_{OSHL} = |t_{PHL}max - t_{PHL}min|$.

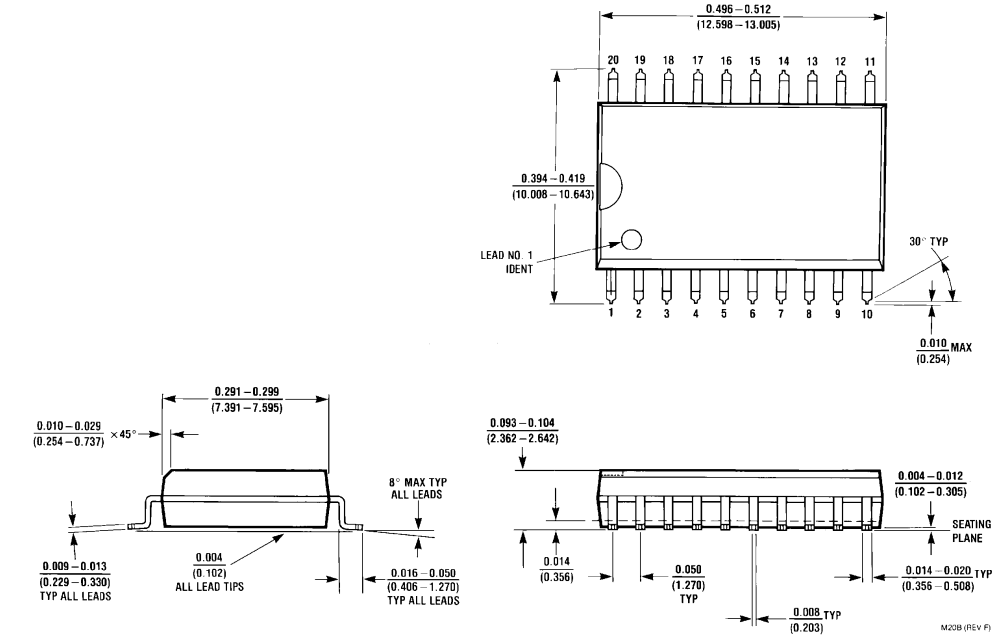
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pieces of the Flip Flop operates can be calculated by the equation: C_{PD} (total) = 22 + 9n.

AC Operating Requirements

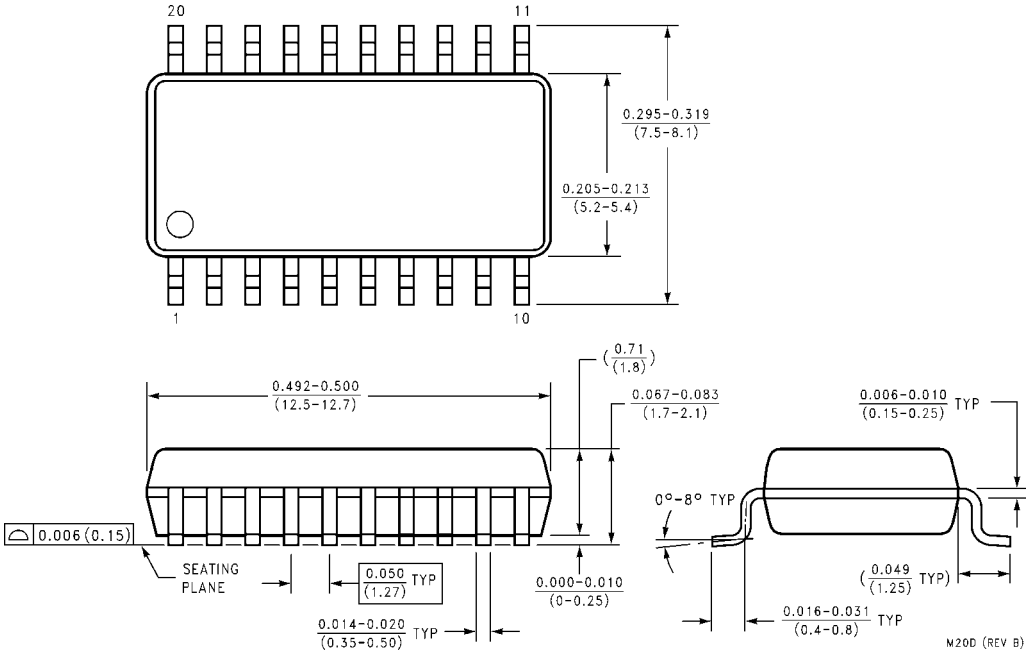
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
$t_W(L)$	Minimum Pulse Width (CK)	3.3		5.5	6.5	ns
$t_W(H)$		5.0		5.0	5.0	
$t_W(L)$	Minimum Pulse Width ($\overline{MR}$)	3.3		5.0	6.0	ns
		5.0		5.0	5.0	
t_S	Minimum Setup Time	3.3		5.5	6.5	ns
		5.0		4.5	4.5	
t_H	Minimum Hold Time	3.3		1.0	1.0	ns
		5.0		1.0	1.0	
t_{REC}	Minimum Removal Time ($\overline{MR}$)	3.3		2.5	2.5	ns
		5.0		2.0	2.0	

Note 6: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

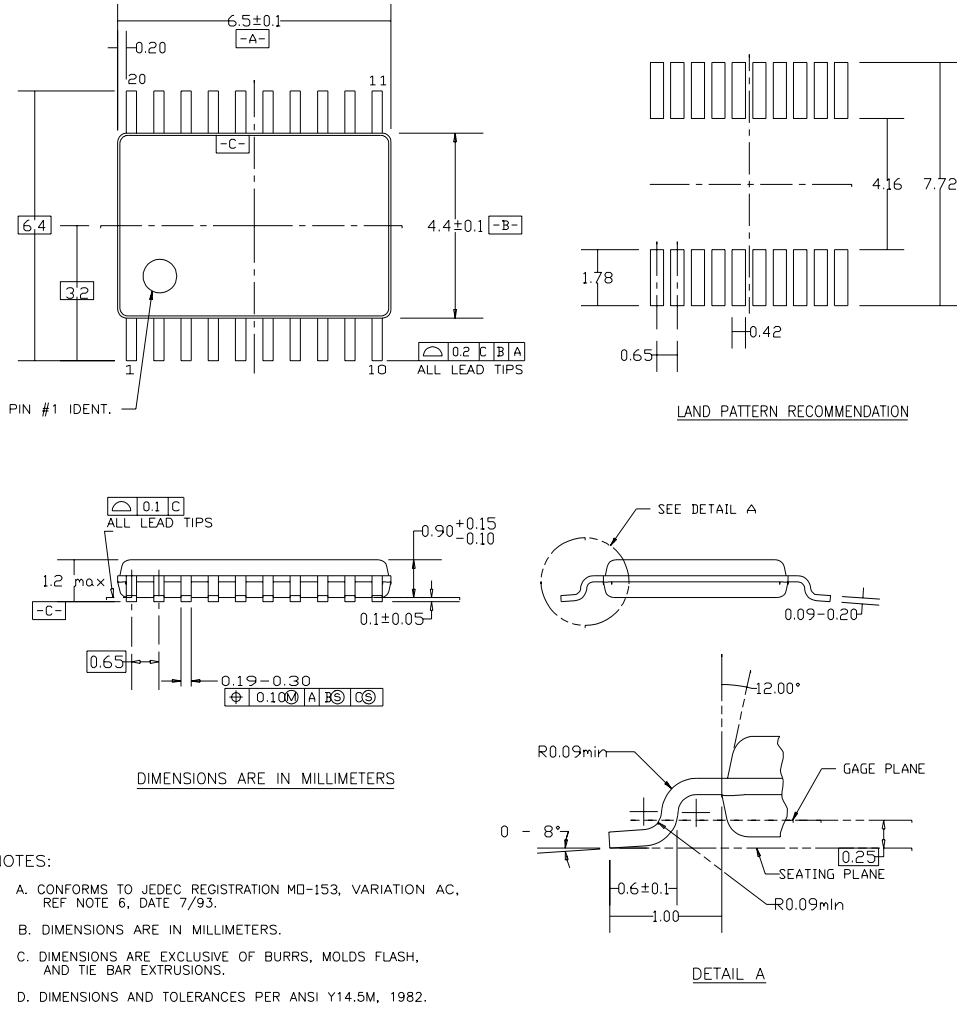


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

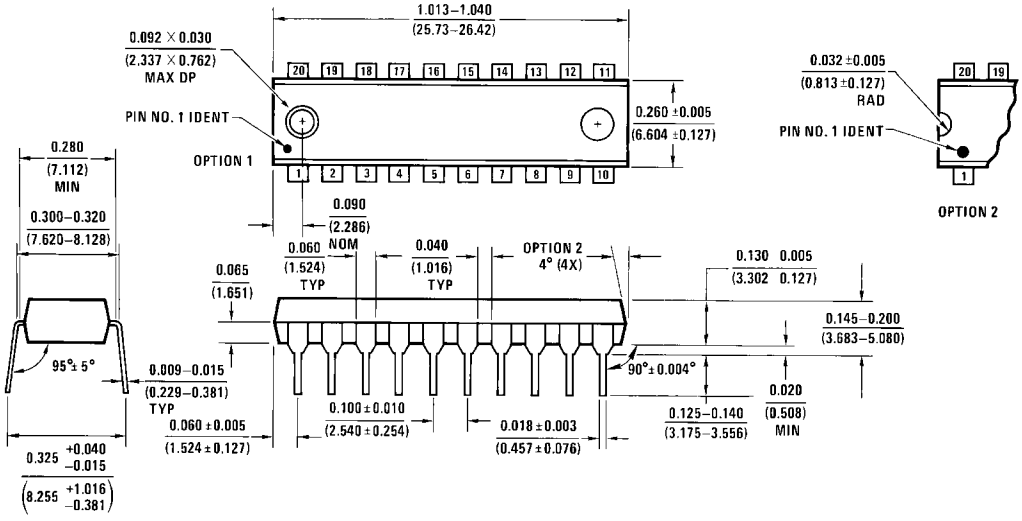
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

National Semiconductor

PRELIMINARY
November 1995

74VHC299
8-Input Universal Shift/Storage Register with Common Parallel I/O Pins

General Description

The VHC299 is an advanced high speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC299 is an 8-bit universal shift/storage register with TRI-STATE® outputs. Four modes of operation are possible: hold (store), shift left, shift right and load data. The parallel load inputs and flip-flop outputs are multiplexed to reduce the total number of package pins. Additional outputs are provided for flip-flops Q_0, Q_7 to allow easy serial cascading. A separate active LOW Master Reset is used to reset the register.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

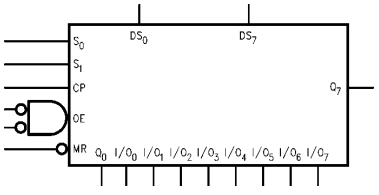
Features

- Low power dissipation: $I_{CC} = 4\ \mu A$ at $T_A = 25°C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\%\ V_{CC}$ (min)
- All inputs are equipped with a power down protection function
- Balanced propagation delays: $t_{PLH} \cong t_{PHL}$
- Low noise: $V_{OLP} = 0.9V$ (typ)
- Pin and function compatible with 74HC299

Commercial	Package Number	Package Description
74VHC299M	M20B	20-Lead Molded JEDEC SOIC
74VHC299SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC299MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHC299N	N20A	20-Lead Molded DIP

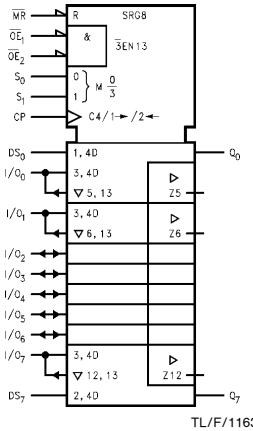
Note: Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter 'X' to the ordering code.

Logic Symbols



TL/F/11638–1

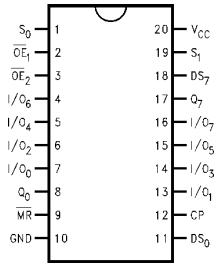
IEEE/IEC



TL/F/11638–3

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



TL/F/11638–2

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Pin Names	Description
CP	Clock Pulse Input
DS_0	Serial Data Input for Right Shift
DS_7	Serial Data Input for Left Shift
S_0, S_1	Mode Select Inputs
$\overline{MR}$	Asynchronous Master Reset
$\overline{OE}_1$, $\overline{OE}_2$	TRI-STATE Output Enable Inputs
I/O_0–I/O_7	Parallel Data Inputs or TRI-STATE Parallel Outputs
Q_0, Q_7	Serial Outputs

Functional Description

The VHC299 contains eight edge-triggered D-type flip-flops and the interstage logic necessary to perform synchronous shift left, shift right, parallel load and hold operations. The type of operation is determined by S_0 and S_1, as shown in the Truth Table. All flip-flop outputs are brought out through TRI-STATE buffers to separate I/O pins that also serve as data inputs in the parallel load mode. Q_0 and Q_7 are also brought out on other pins for expansion in serial shifting of longer words.

A LOW signal on $\overline{MR}$ overrides the Select and CP inputs and resets the flip-flops. All other state changes are initiated by the rising edge of the clock. Inputs can change when the clock is in either state provided only that the recommended setup and hold times, relative to the rising edge of CP, are observed.

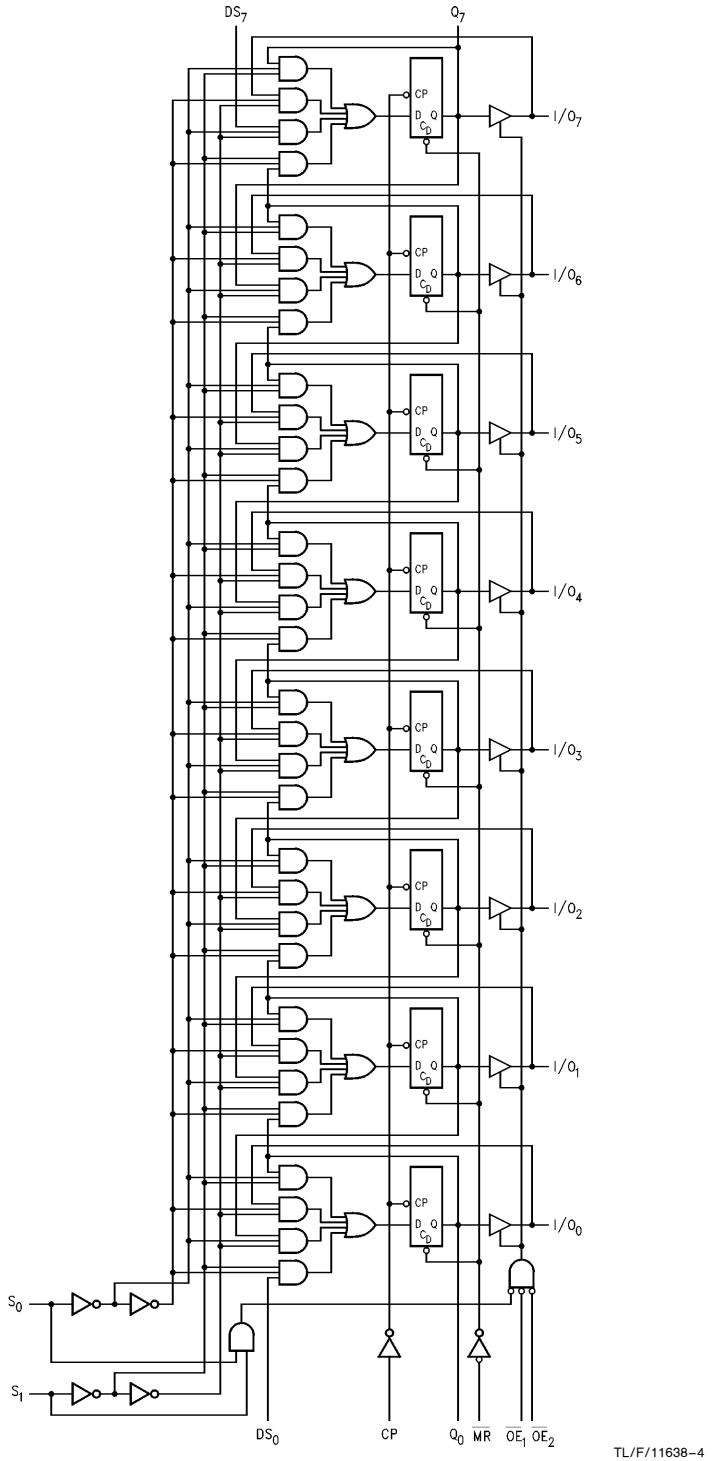
A HIGH signal on either $\overline{OE}_1$ or $\overline{OE}_2$ disables the TRI-STATE buffers and puts the I/O pins in the high impedance state. In this condition the shift, hold, load and reset operations can still occur. The TRI-STATE buffers are also disabled by HIGH signals on both S_0 and S_1 in preparation for a parallel load operation.

Truth Table

Inputs				Response
$\overline{MR}$	S_1	S_0	CP	
L	X	X	X	Asynchronous Reset; Q_0–Q_7 = LOW
H	H	H	⌐⌐	Parallel Load; $I/O_n \rightarrow Q_n$
H	L	H	⌐⌐	Shift Right; $DS_0 \rightarrow Q_0$, $Q_0 \rightarrow Q_1$, etc.
H	H	L	⌐⌐	Shift Left, $DS_7 \rightarrow Q_7$, $Q_7 \rightarrow Q_6$, etc.
H	L	L	X	Hold

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐⌐ = LOW-to-HIGH Transition

Logic Diagram



TL/F/11638–4

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C

Note 1: *Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation outside databook specifications.*

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

DC Characteristics for 'VHC Family Devices

Symbol	Parameter	V_{CC} (V)	74VHC					Units	Conditions	
			T_A = +25°C			T_A = −40°C to +85°C				
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0 3.0–5.5	1.50 0.7 V_{CC}			1.50 0.7 V_{CC}		V		
V_{IL}	Low Level Input Voltage	2.0 3.0–5.5			0.50 0.3 V_{CC}		0.50 0.3 V_{CC}	V		
V_{OH}	High Level Output Voltage	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0 4.5	2.58 3.94			2.48 3.80		V		I_{OH} = −4 mA I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0 4.5			0.36 0.36		0.44 0.44	V		I_{OL} = 4 mA I_{OL} = 8 mA
I_{OZ}	TRI-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

DC Characteristics for 'VHC Family Devices:

Symbol	Parameter	V_{CC} (V)	74VHC $T_A = +25°C$		Units	Conditions
			Typ	Limits		
V_{OLP}**	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	$C_L = 50$ pF
V_{OLV}**	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.9	−1.2	V	$C_L = 50$ pF
V_{IHD}**	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	$C_L = 50$ pF
V_{ILD}**	Maximum High Level Dynamic Input Voltage	5.0		1.5	V	$C_L = 50$ pF

**Parameter guaranteed by design.

AC Electrical Characteristics for 'VHC Family Devices:

Symbol	Parameter	V_{CC} (V)	74VHC $T_A = +25°C$			74VHC $T_A = -40°C$ to $+85°$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH} t_{PHL}	Propagation Delay Time CP to Q_0 or Q_7 (Shift Left or Right)	3.3 ±0.3		12.2	17.2	1.0	19.8	ns		$C_L = 15$ pF
				14.7	20.7	1.0	23.3			$C_L = 50$ pF
		5.0 ±0.5		8.5	10.8	1.0	12.0	ns		$C_L = 15$ pF
				10.0	12.8	1.0	14.0			$C_L = 50$ pF
t_{PLH} t_{PHL}	Propagation Delay Time (CP − I/O_n)	3.3 ±0.3		10.3	14.3	1.0	16.6	ns		$C_L = 15$ pF
				12.8	17.8	1.0	20.1			$C_L = 50$ pF
		5.0 ±0.5		7.3	9.1	1.0	10.4	ns		$C_L = 15$ pF
				8.8	11.1	1.0	12.4			$C_L = 50$ pF
t_{PHL}	Propagation Delay Time ($\overline{MR}$ to Q_0 or Q_7)	3.3 ±0.3		13.0	19.0	1.0	22.0	ns		$C_L = 15$ pF
				15.5	22.5	1.0	25.5			$C_L = 50$ pF
		5.0 ±0.5		9.1	11.2	1.0	13.5	ns		$C_L = 15$ pF
				10.8	13.2	1.0	15.5			$C_L = 50$ pF
t_{PHL}	Propagation Delay Time ($\overline{MR}$ − I/O_n)	3.3 ±0.3		10.8	17.0	1.0	19.5	ns		$C_L = 15$ pF
				13.3	20.5	1.0	23.0			$C_L = 50$ pF
		5.0 ±0.5		7.7	10.5	1.0	12.0	ns		$C_L = 15$ pF
				9.2	12.5	1.0	14.0			$C_L = 50$ pF
t_{PZL} t_{PZH}	Output Enable Time ($\overline{OE}$ − I/O_n)	3.3 ±0.3		13.3	16.5	1.0	19.2	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
				14.8	19.0	1.0	21.7			$C_L = 50$ pF
		5.0 ±0.5		8.9	9.7	1.0	11.3	ns		$C_L = 15$ pF
				10.4	11.2	1.0	12.6			$C_L = 50$ pF
t_{PZL} t_{PZH}	Output Enable Time (S_0 or S_1 to I/O_n)	3.3 ±0.3		13.3	16.5	1.0	19.2	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
				14.8	19.0	1.0	21.7			$C_L = 50$ pF
		5.0 ±0.5		8.9	9.7	1.0	11.3	ns		$C_L = 15$ pF
				10.4	11.2	1.0	12.6			$C_L = 50$ pF
t_{PLZ} t_{PHZ}	Output Disable Time ($\overline{OE}$ − I/O_n)	3.3 ±0.3		18.0	21.3	1.0	24.3	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
		5.0 ±0.5		11.8	13.2	1.0	15.0			$C_L = 50$ pF
t_{PLZ} t_{PHZ}	Output Disable Time (S_0 or S_1 to I/O_n)	3.3 ±0.3		18.0	21.3	1.0	24.3	ns	$R_L = 1$ kΩ	$C_L = 50$ pf
		5.0 ±0.5		11.8	13.2	1.0	15.0			$C_L = 50$ pF
f_{MAX}	Maximum Clock Frequency	3.3 ±0.3	65	100		55		MHz		$C_L = 15$ pF
			55	90		50				$C_L = 50$ pF
		5.0 ±0.5	125	160		110		MHz		$C_L = 15$ pF
			115	150		100				$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			4				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			110				pF	(Note 1)	

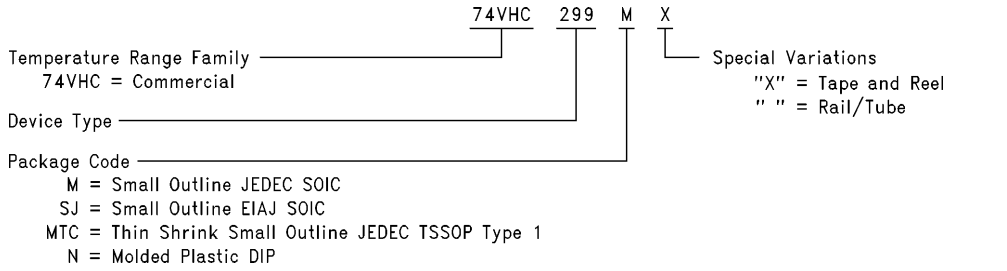
Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

AC Operating Requirements for 'VHC Family Devices:

Symbol	Parameter	V_{CC} (V)	74VHC $T_A = +25°C$		74VHC $T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits			
t_S	Minimum Setup Time S_0 or S_1 to CP	3.3 ±0.3 5.0 ±0.5		14.5 7.0	17.0 8.0	ns	
t_S	Minimum Setup Time I/O_n to CP	3.3 ±0.3 5.0 ±0.5		8.0 4.0	9.0 4.0	ns	
t_S	Minimum Setup Time DS_0 or DS_7 to CP	3.3 ±0.3 5.0 ±0.5		8.5 5.0	10.0 5.0	ns	
t_H	Minimum Hold Time S_0 or S_1 to CP	3.3 ±0.3 5.0 ±0.5		0.0 0.5	0.0 0.5	ns	
t_H	Minimum Hold Time I/O_n to CP	3.3 ±0.3 5.0 ±0.5		0.5 1.5	0.5 1.5	ns	
t_H	Minimum Hold Time DS_0 or DS_7 to CP	3.3 ±0.3 5.0 ±0.5		1.0 1.0	1.0 1.0	ns	
$t_{W(L)}$ $t_{W(H)}$	Minimum Pulse Width (CP)	3.3 ±0.3 5.0 ±0.5		7.0 7.0	8.0 8.0	ns	
$t_{W(L)}$	Minimum Pulse Width ($\overline{MR}$)	3.3 ±0.3 5.0 ±0.5		6.0 6.0	7.0 7.0	ns	
t_{rem}	Minimum Removal Time ($\overline{MR}$ to CP)	3.3 ±0.3 5.0 ±0.5		5.0 4.0	6.0 4.0	ns	

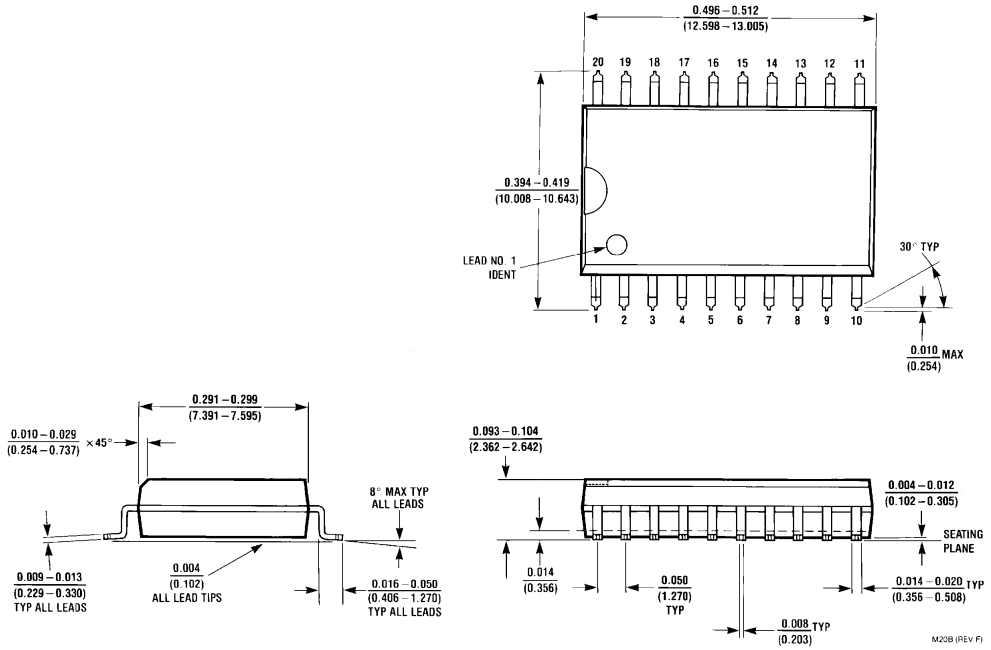
Ordering Information

The device number is used to form part of a simplified purchasing code, where the package type and temperature range are defined as follows:

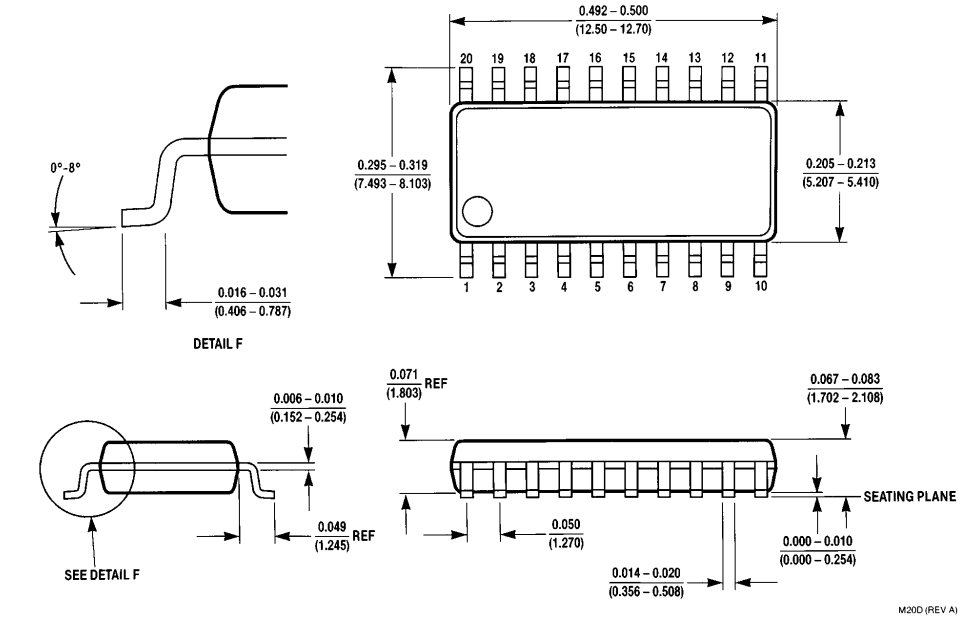


TL/F/11638–5

Physical Dimensions inches (millimeters)

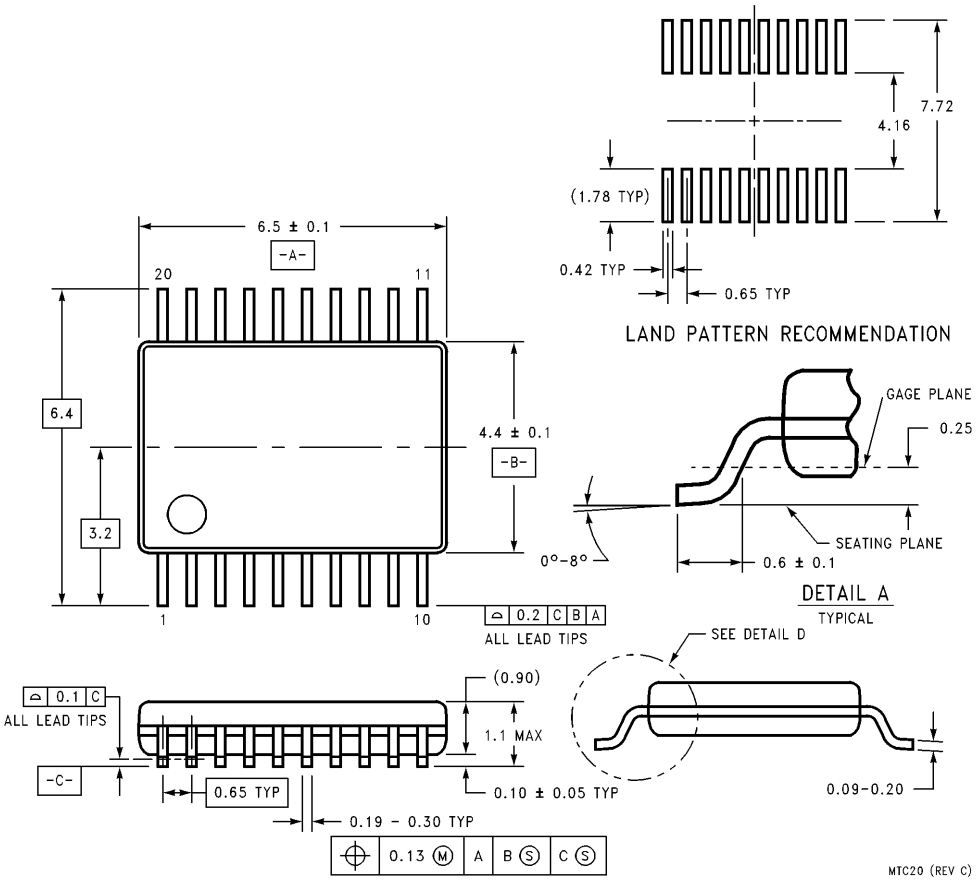


20-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Order Number 74VHC299M or 74VHC299MX
NS Package Number M20B



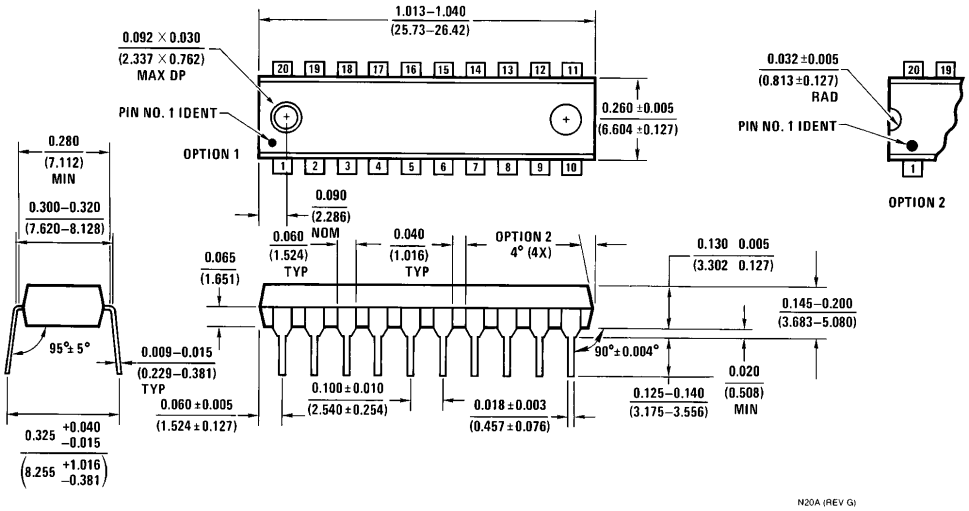
20-Lead Plastic EIAJ SOIC (SJ)
Order Number 74VHC299SJ or 74VHC299SJX
NS Package Number M20D

Physical Dimensions inches (millimeters) (Continued)



20-Lead Molded Thin Shrink Small Outline JEDEC Type I TSSOP
Order Number 74VHC299MTC
NS Package Number MTC20

Physical Dimensions inches (millimeters) (Continued)



20-Lead Molded Dual-In-Line Package
Order Number 74VHC299N
NS Package Number N20A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised March 1999

74VHC32
Quad 2-Input OR Gate

General Description

The VHC32 is an advanced high speed CMOS 2-Input OR Gate fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

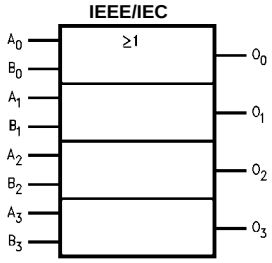
- High Speed:
  t_{PD} = 3.8 ns (typ) at V_{CC} = 5V
- Low Power Dissipation:
  I_{CC} = 2 μA (Max) at T_A = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low Noise: V_{OLP} = 0.8V (Max)
- Pin and Function Compatible with 74HC32

Ordering Code:

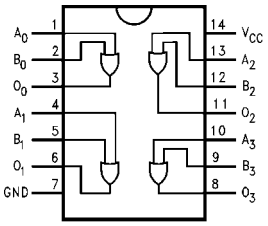
Order Number	Package Number	Package Description
74VHC32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VHC32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Truth Table

A	B	O
H	H	H
L	H	H
H	L	H
L	L	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

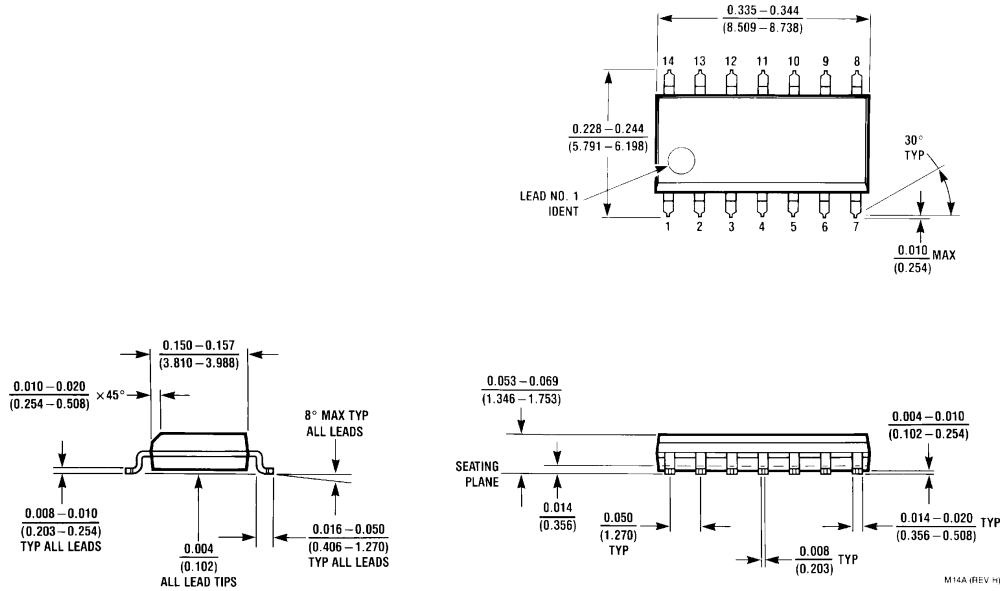
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

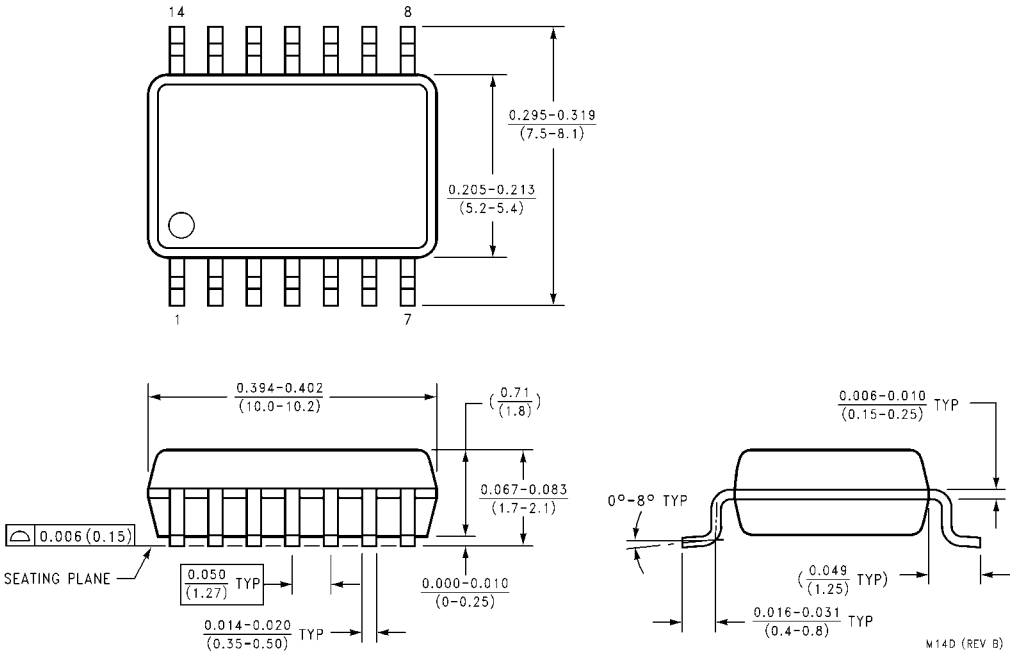
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL}	Propagation Delay	3.3		5.5	7.9	1.0	9.5	ns	C_L = 15 pF
t_{PLH}		±0.3		8.0	11.4	1.0	13.0		C_L = 50 pF
		5.0		3.8	5.5	1.0	6.5	ns	C_L = 15 pF
		±0.5		5.3	7.5	1.0	8.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			14				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

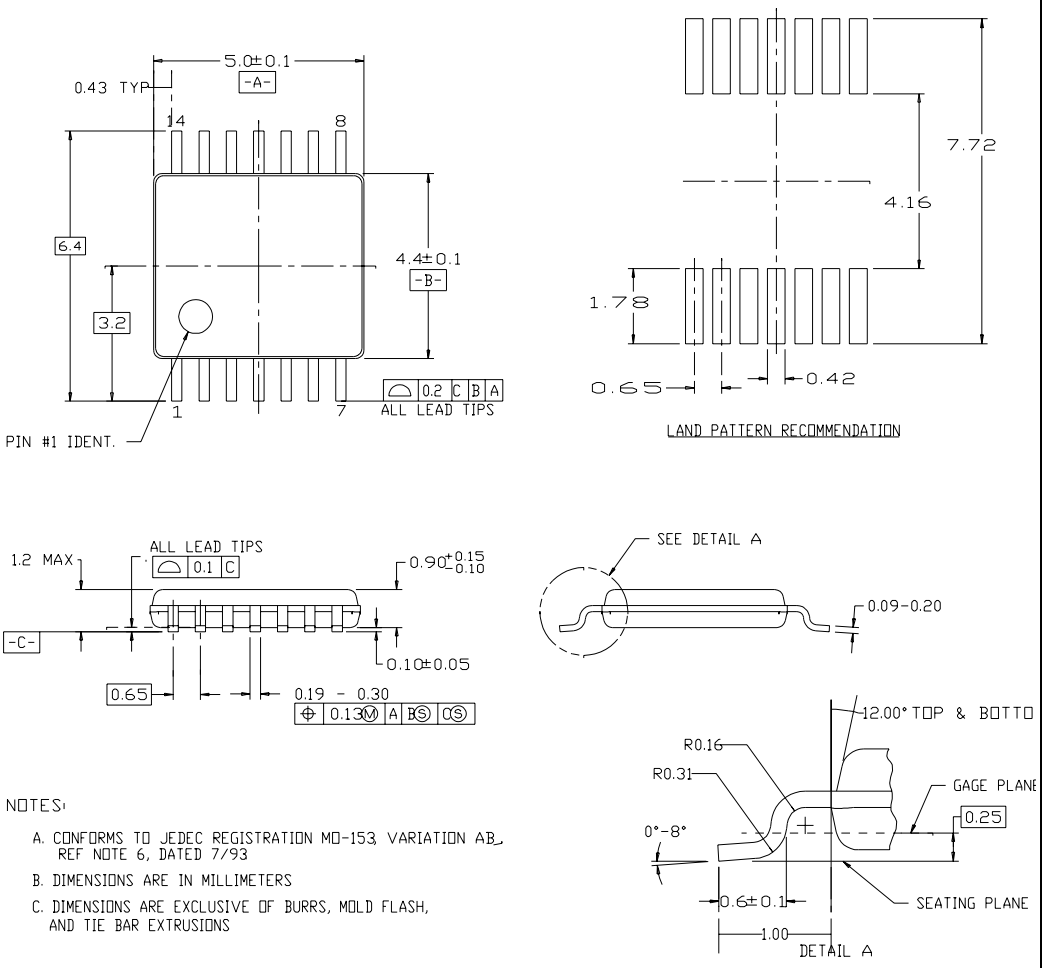


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

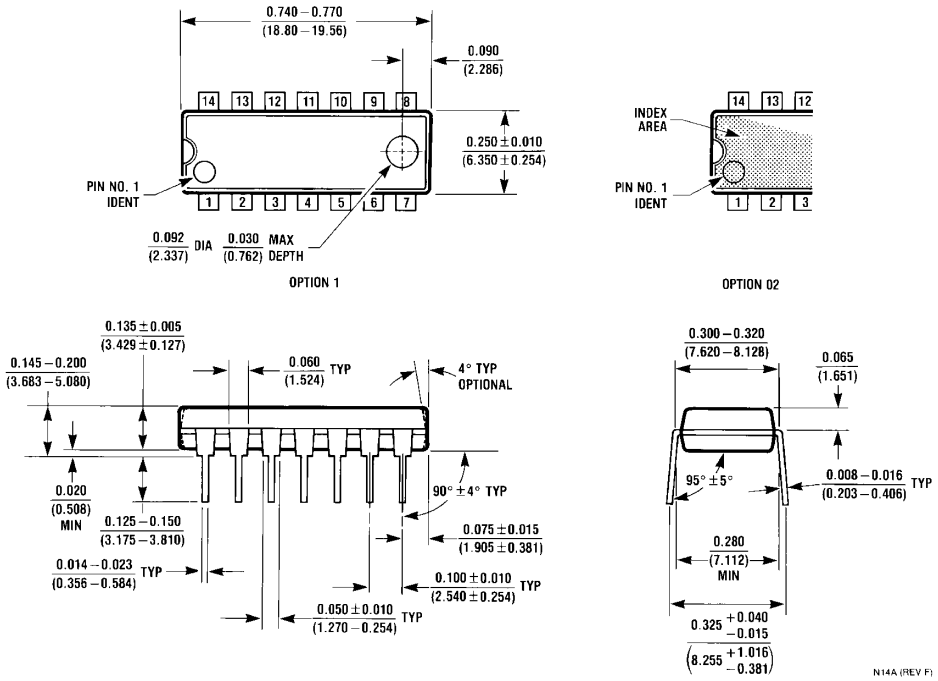
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

February 1993
Revised April 1999

74VHC373
Octal D-Type Latch with 3-STATE Outputs

General Description

The VHC373 is an advanced high speed CMOS octal D-type latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ($\overline{OE}$). The latches appear transparent to data when latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is LATCHED. When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

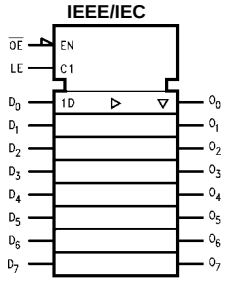
- High Speed: t_{PD} = 5.0 ns (typ) @ V_{CC} = 5V
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power Down Protection is provided on all inputs
- Low Noise: V_{OLP} = 0.6V (typ)
- Low Power Dissipation: I_{CC} = 4 µA (Max) @ T_A = 25°C
- Pin and Function Compatible with 74HC373

Ordering Code:

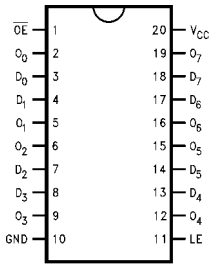
Order Number	Package Number	Package Description
74VHC373M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC373SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC373MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC373N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

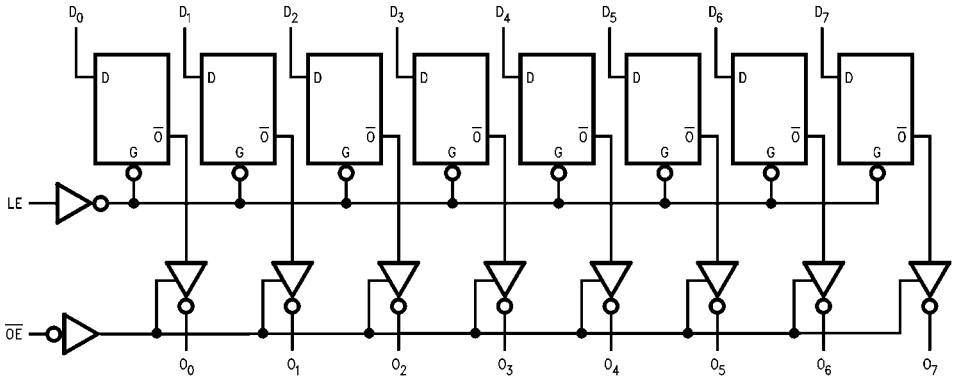
The VHC373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to + 7.0V
DC Input Voltage (V_{IN})	−0.5V to + 7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to + 5.5V
Input Voltage (V_{IN})	0V to + 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0 ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0			0.50		0.50	V		
	Input Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
	Output Voltage	3.0	2.9	3.0		2.9			or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1		or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5 or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		7.0	11.0	1.0	13.0	ns		C_L = 15 pF
t_{PHL}	Time (LE to O_n)			9.5	14.5	1.0	16.5			C_L = 50 pF
		5.0 ± 0.5		4.9	7.2	1.0	8.5	ns		C_L = 15 pF
				6.4	9.2	1.0	10.5			C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		7.3	11.4	1.0	13.5	ns		C_L = 15 pF
t_{PHL}	Time (D to O_n)			9.8	14.9	1.0	17.0			C_L = 50 pF
		5.0 ± 0.5		5.0	7.2	1.0	8.5			C_L = 15 pF
				6.5	9.2	1.0	10.5			C_L = 50 pF
t_{PZL}	3-STATE	3.3 ± 0.3		7.3	11.4	1.0	13.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Output			9.8	14.9	1.0	17.0			C_L = 50 pF
	Enable Time	5.0 ± 0.5		5.5	8.1	1.0	9.5	ns		C_L = 15 pF
				7.0	10.1	1.0	11.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		9.5	13.2	1.0	15.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ± 0.5		6.5	9.2	1.0	10.5			C_L = 50 pF
t_{OSLH}	Output to	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C_L = 50 pF
t_{OSHL}	Output Skew	5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			27				pF	(Note 5)	

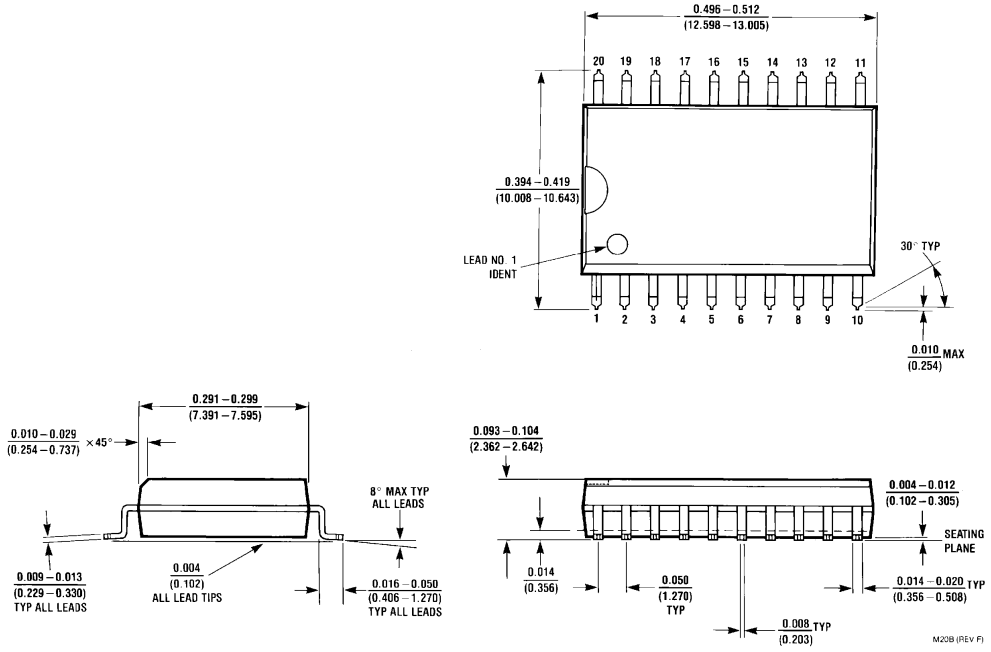
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL}\ min|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per Latch). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 14 + 13n.

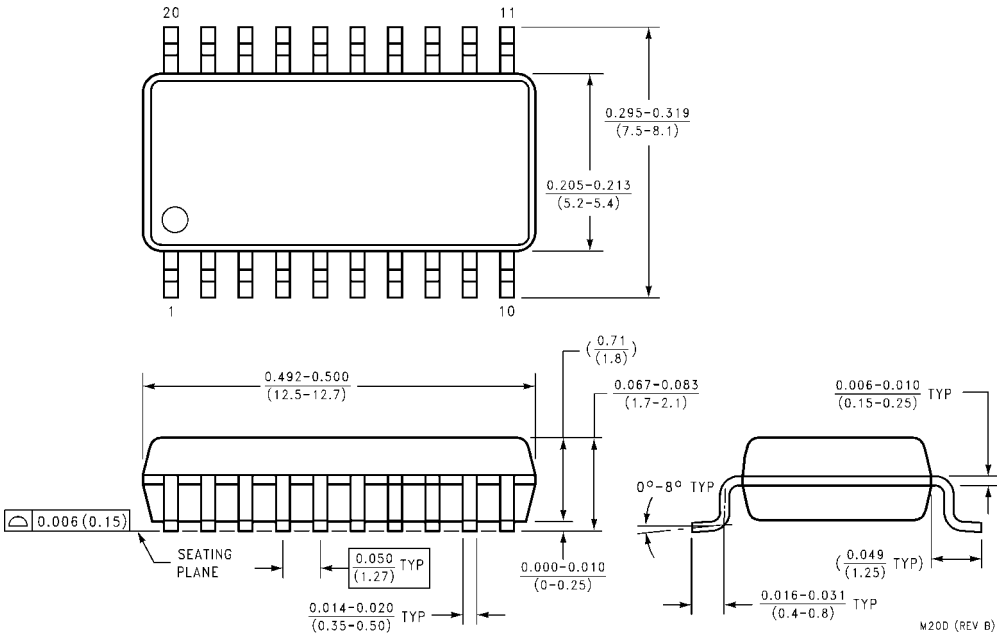
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
t_W(H)	Minimum Pulse Width (LE)	3.3 ± 0.3	5.0			5.0		ns
		5.0 ± 0.5	5.0			5.0		
t_S	Minimum Set-Up Time	3.3 ± 0.3	4.0			4.0		ns
		5.0 ± 0.5	4.0			4.0		
t_H	Minimum Hold Time	3.3 ± 0.3	1.0			1.0		ns
		5.0 ± 0.5	1.0			1.0		

Physical Dimensions inches (millimeters) unless otherwise noted

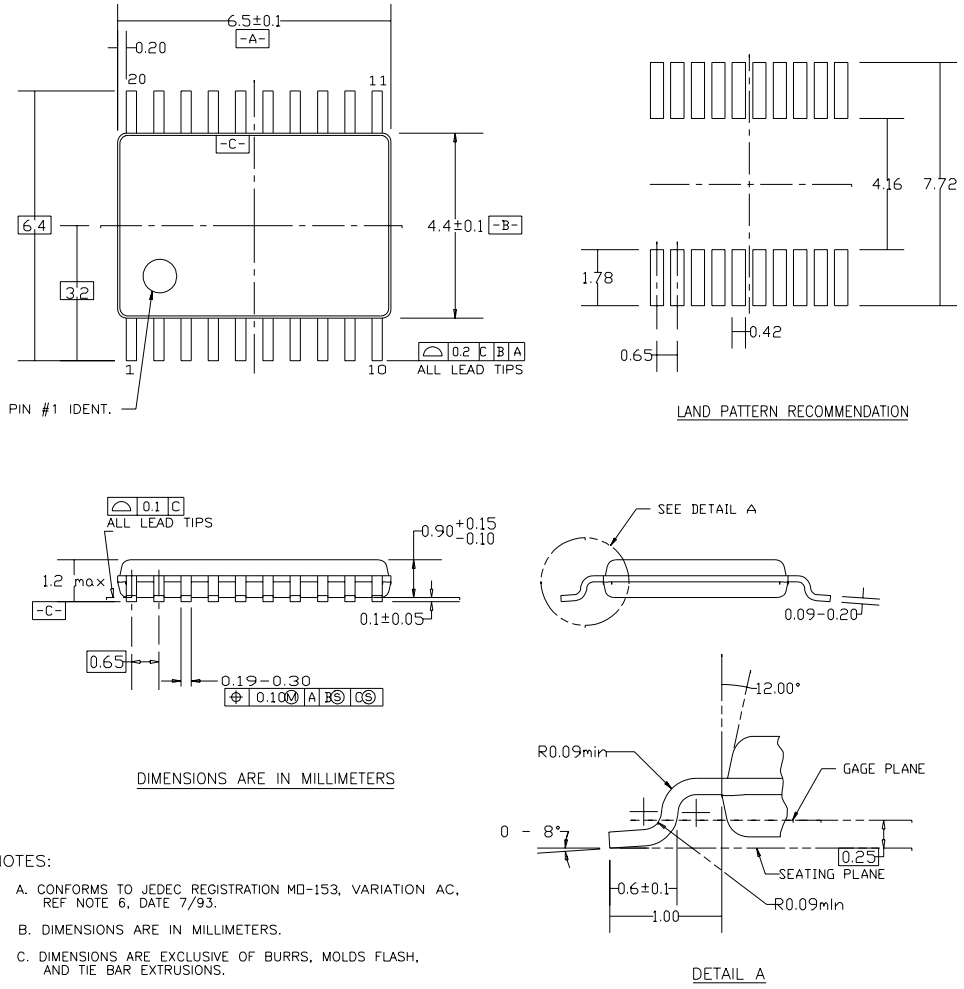


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

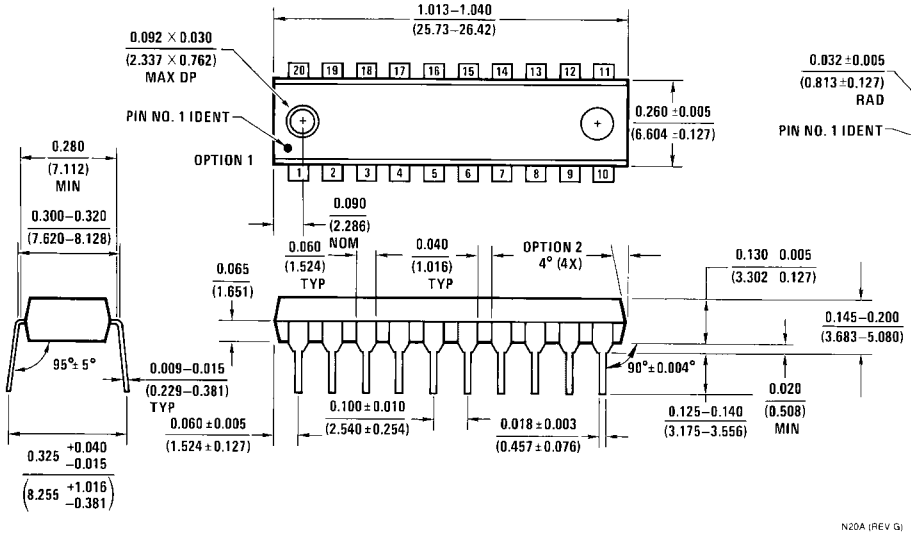
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

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November 1992
Revised April 1999

74VHC374
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The VHC374 is an advanced high speed CMOS octal flip-flop with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type flip-flop is controlled by a clock input (CP) and an output enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a HIGH impedance state.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

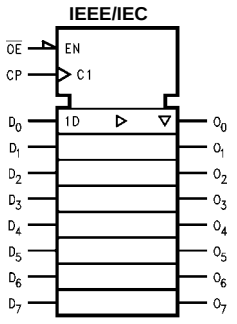
- High Speed: t_{PD} = 5.4 ns (typ) at V_{CC} = 5V
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low power dissipation: I_{CC} = 4 μA (Max) @ T_A = 25°C
- Pin and function compatible with 74HC374

Ordering Code:

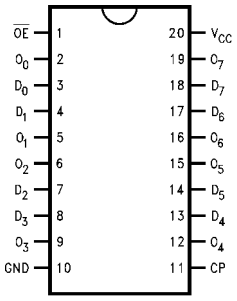
Order Number	Package Number	Package Description
74VHC374M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300” Wide
74VHC374SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC374N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

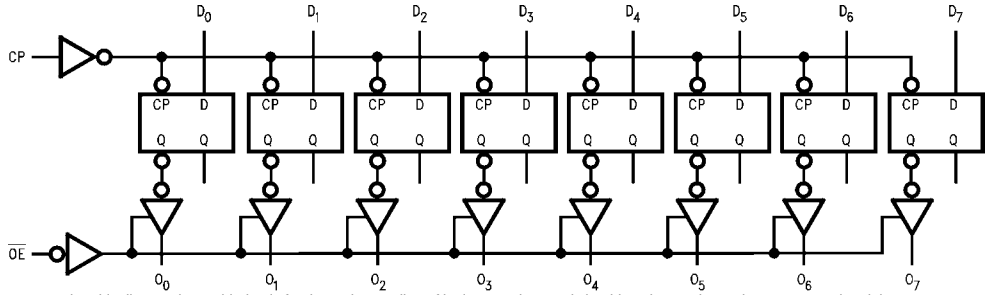
The VHC374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V – 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V – 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time	3.3 ± 0.3		8.1	12.7	1.0	15.0	ns		$C_L = 15$ pF
t_{PHL}	(CP to O_n)			10.6	16.2	1.0	18.5			$C_L = 50$ pF
		5.0 ± 0.5		5.4	8.1	1.0	9.5	ns		$C_L = 15$ pF
				6.9	10.1	1.0	11.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		7.1	11.0	1.0	13.0	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			9.6	14.5	1.0	16.5			$C_L = 50$ pF
		5.0 ± 0.5		5.1	7.6	1.0	9.0	ns		$C_L = 15$ pF
				6.6	9.6	1.0	11.0			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		10.2	14.0	1.0	16.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time	5.0 ± 0.5		6.1	8.8	1.0	10.0			$C_L = 50$ pF
t_{OSLH}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	$C_L = 50$ pF
t_{OSHL}		5.0 ± 0.5			1.0		1.0			$C_L = 50$ pF
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	80	130		70		MHz		$C_L = 15$ pF
			55	85		50				$C_L = 50$ pF
		5.0 ± 0.5	130	185		110				$C_L = 15$ pF
			85	120		75				$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			32				pF	(Note 5)	

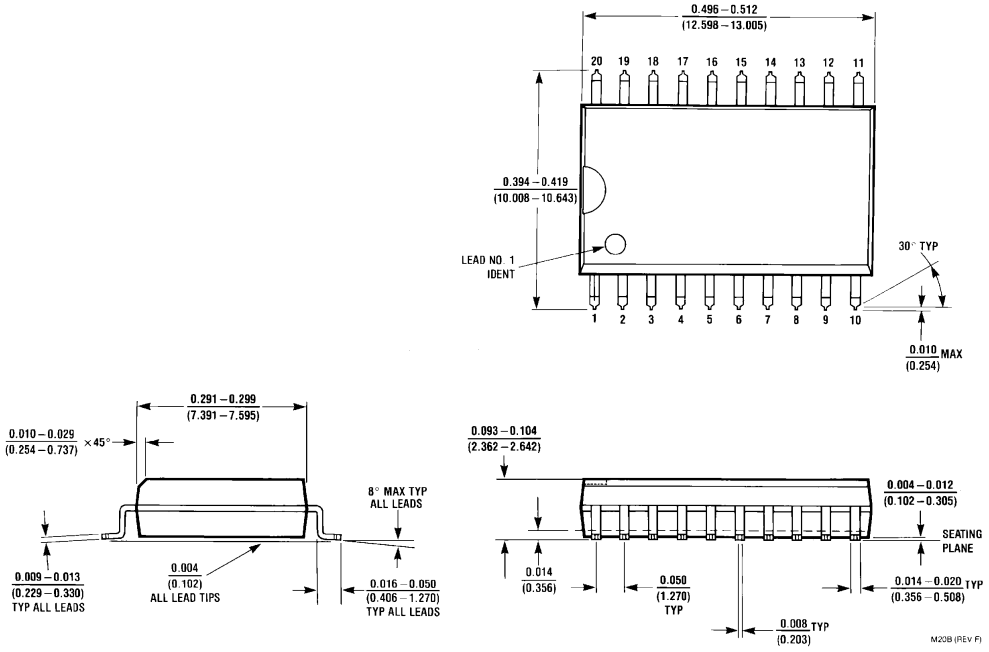
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

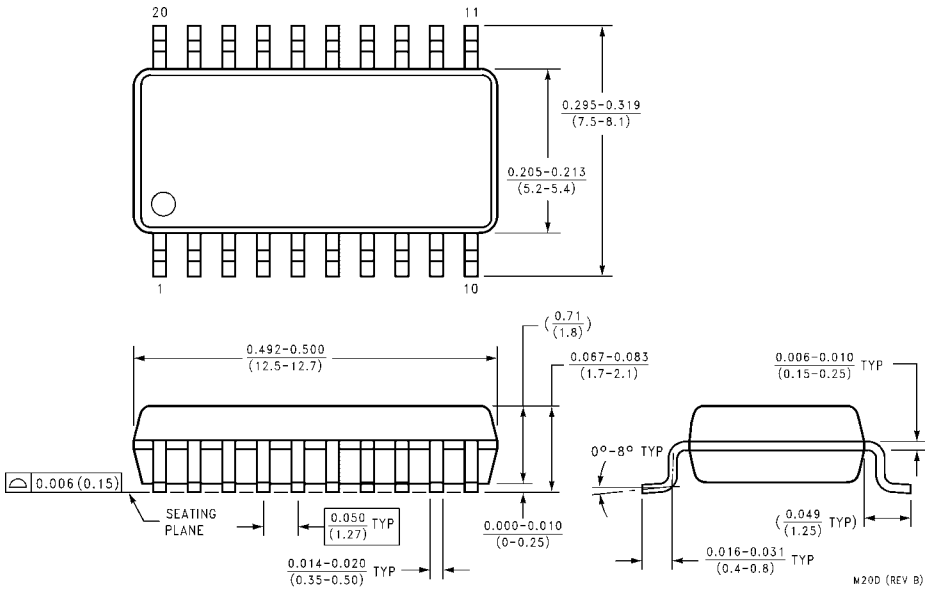
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
$t_W(H)$	Minimum Pulse Width (CP)	3.3 ± 0.3	5.0			5.5		ns
$t_W(L)$		5.0 ± 0.5	5.0			5.0		
t_S	Minimum Set-Up Time	3.3 ± 0.3	4.5			4.5		ns
		5.0 ± 0.5	3.0			3.0		
t_H	Minimum Hold Time	3.3 ± 0.3	2.0			2.0		ns
		5.0 ± 0.5	2.0			2.0		

Physical Dimensions inches (millimeters) unless otherwise noted

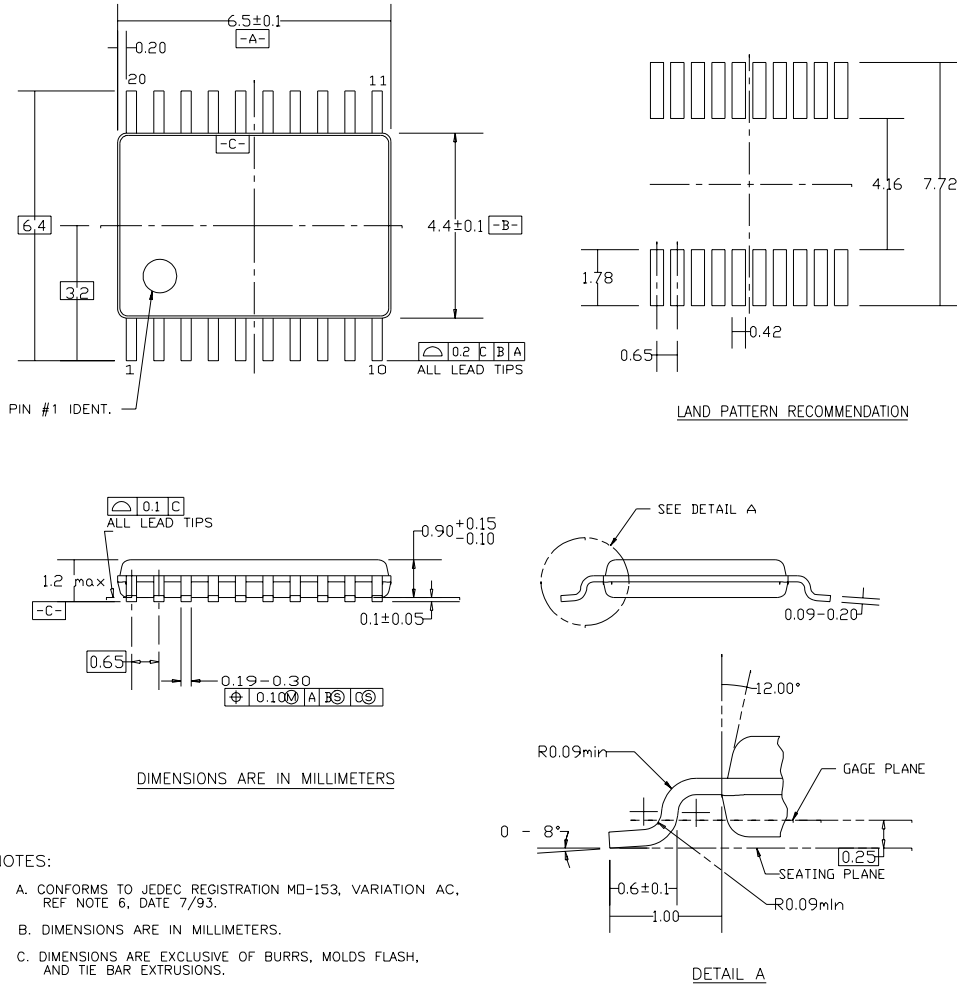


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

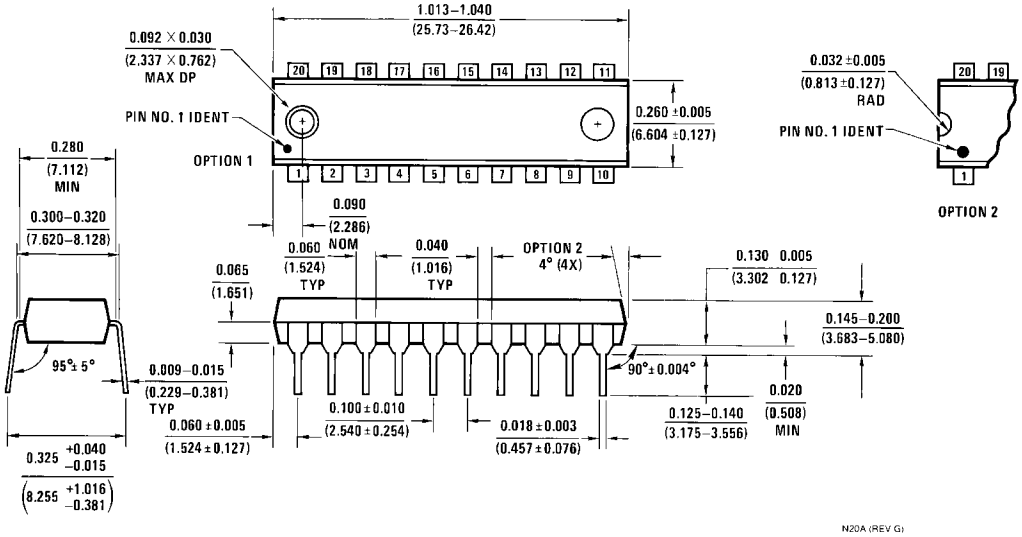
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1993
Revised March 1999

74VHC393
Dual 4-Bit Binary Counter

General Description

The VHC393 is an advanced high speed CMOS 4-bit Binary Counter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. It contains two independent counter circuits in one package, so that counting or frequency division of 8 binary bits can be achieved with one IC. This device changes state on the negative going transition of the CLOCK pulse. The counter can be reset to "0" (Q_0–Q_3 = "L") by a HIGH at the CLEAR input regardless of other inputs.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

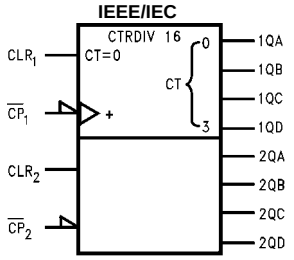
- High Speed: f_{MAX} = 170 MHz (typ) at T_A = 25°C
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC393

Ordering Code:

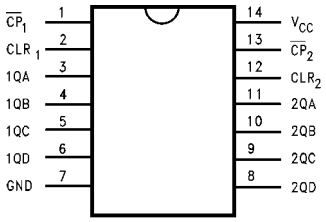
Order Number	Package Number	Package Description
74VHC393M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VHC393SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC393MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC393N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

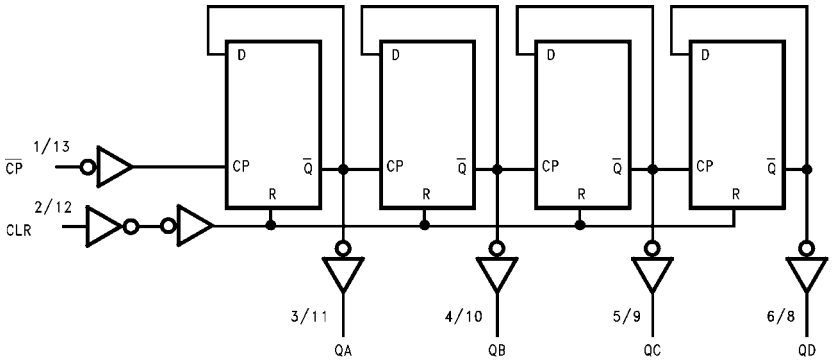
Pin Names	Description
CLR1, CLR2	Clear Inputs
$\overline{CP}_1$, $\overline{CP}_2$	Clock Pulse Inputs
QA, QB, QC, QD	Outputs

Truth Table

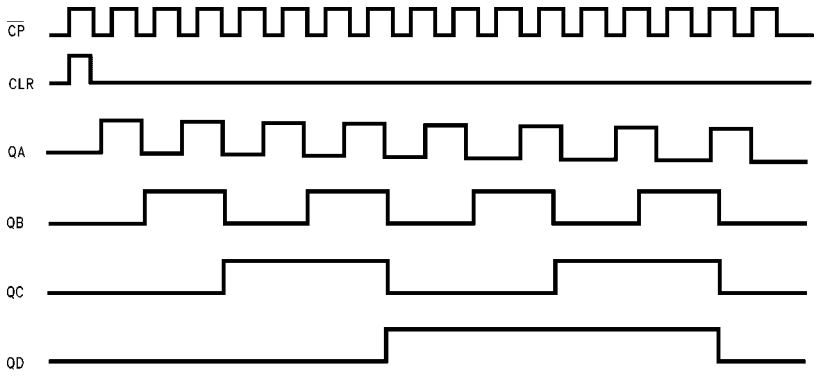
Inputs		Outputs			
$\overline{CP}$	CLR	QA	QB	QC	QD
X	H	L	L	L	L
↓	L	Count Up			
↑	L	No Change			

X: Don't Care

System Diagram



Timing Chart



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

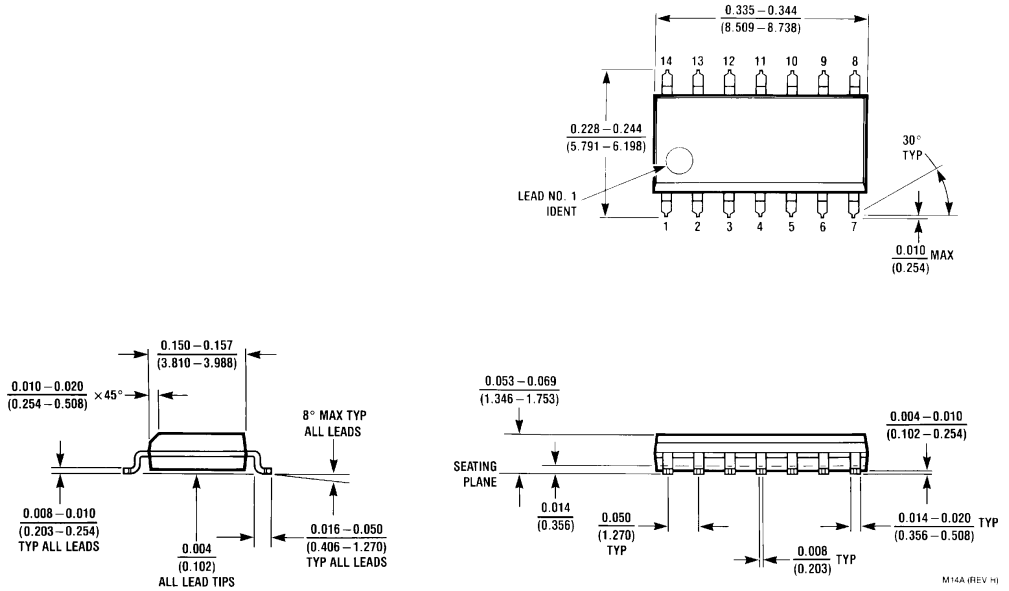
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation	3.3 ± 0.3		8.6	13.2	1.0	15.5	ns		C_L = 15 pF
t_{PHL}	Delay Time			11.1	16.7	1.0	19.0			C_L = 50 pF
	($\overline{CP}$ -QA)	5.0 ± 0.5		5.8	8.5	1.0	10.0	ns		C_L = 15 pF
				7.3	10.5	1.0	12.0			C_L = 50 pF
t_{PLH}	Propagation	3.3 ± 0.3		10.2	15.8	1.0	18.5	ns		C_L = 15 pF
t_{PHL}	Delay Time			12.7	19.3	1.0	22.0			C_L = 50 pF
	($\overline{CP}$ -QB)	5.0 ± 0.5		6.8	9.8	1.0	11.5	ns		C_L = 15 pF
				8.3	11.8	1.0	13.5			C_L = 50 pF
t_{PLH}	Propagation	3.3 ± 0.3		11.7	18.0	1.0	21.0	ns		C_L = 15 pF
t_{PHL}	Delay Time			14.2	21.5	1.0	24.5			C_L = 50 pF
	($\overline{CP}$ -QC)	5.0 ± 0.5		7.7	11.2	1.0	13.0	ns		C_L = 15 pF
				9.2	13.2	1.0	15.0			C_L = 50 pF
t_{PLH}	Propagation	3.3 ± 0.3		13.0	19.7	1.0	23.0	ns		C_L = 15 pF
t_{PHL}	Delay Time			15.5	23.2	1.0	26.5			C_L = 50 pF
	($\overline{CP}$ -QD)	5.0 ± 0.5		8.5	12.5	1.0	14.5	ns		C_L = 15 pF
				10.0	14.5	1.0	16.5			C_L = 50 pF
t_{PLH}	Propagation	3.3 ± 0.3		7.9	12.3	1.0	14.5	ns		C_L = 15 pF
t_{PHL}	Delay Time			10.4	15.8	1.0	18.0			C_L = 50 pF
	(CLR-Q_n)	5.0 ± 0.5		5.4	8.1	1.0	9.5	ns		C_L = 15 pF
				6.9	10.1	1.0	11.5			C_L = 50 pF
f_{MAX}	Maximum	3.3 ± 0.3	75	120		65		MHz		C_L = 15 pF
	Clock		45	65		35				C_L = 50 pF
		5.0 ± 0.5	125	170		105				C_L = 15 pF
			85	115		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{PD}	Power Dissipation Capacitance			23				pF	(Note 3)	

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load Average operating current can be obtained by the equation: $I_{CC}(opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC/2}$ (per Counter)

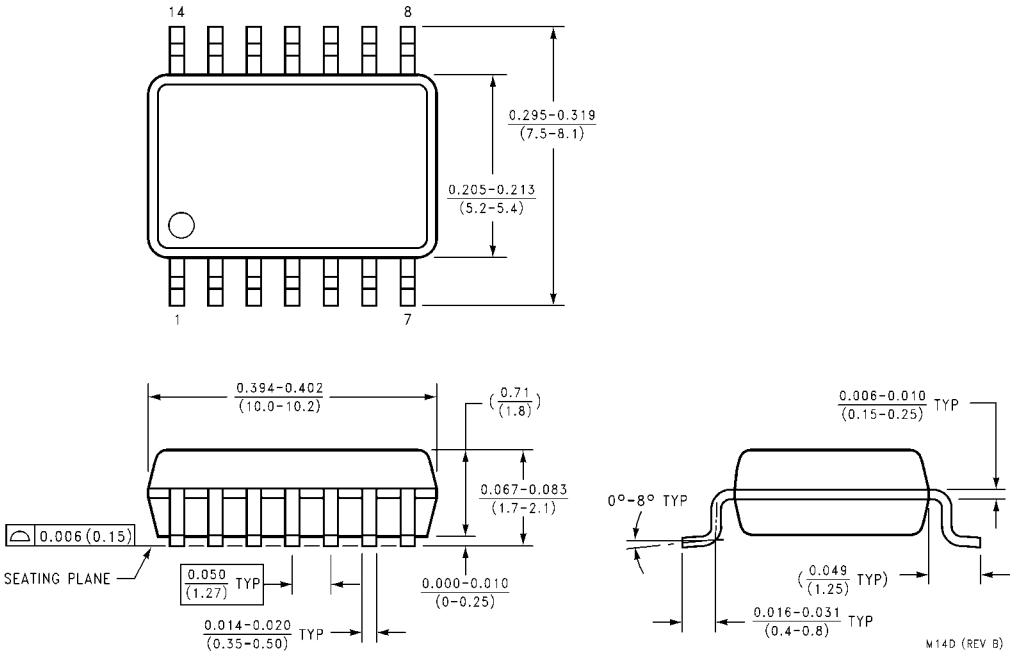
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
$t_W(L)$	Minimum Pulse	3.3 ± 0.3		5.0	5.0	ns
$t_W(H)$	Width ($\overline{CP}$)	5.0 ± 0.5		5.0	5.0	
$t_W(H)$	Minimum Pulse	3.3 ± 0.3		5.0	5.0	ns
	Width (CLR)	5.0 ± 0.5		5.0	5.0	
t_{REM}	Minimum Removal	3.3 ± 0.3		5.0	5.0	ns
	Time	5.0 ± 0.5		4.0	4.0	

Physical Dimensions inches (millimeters) unless otherwise noted



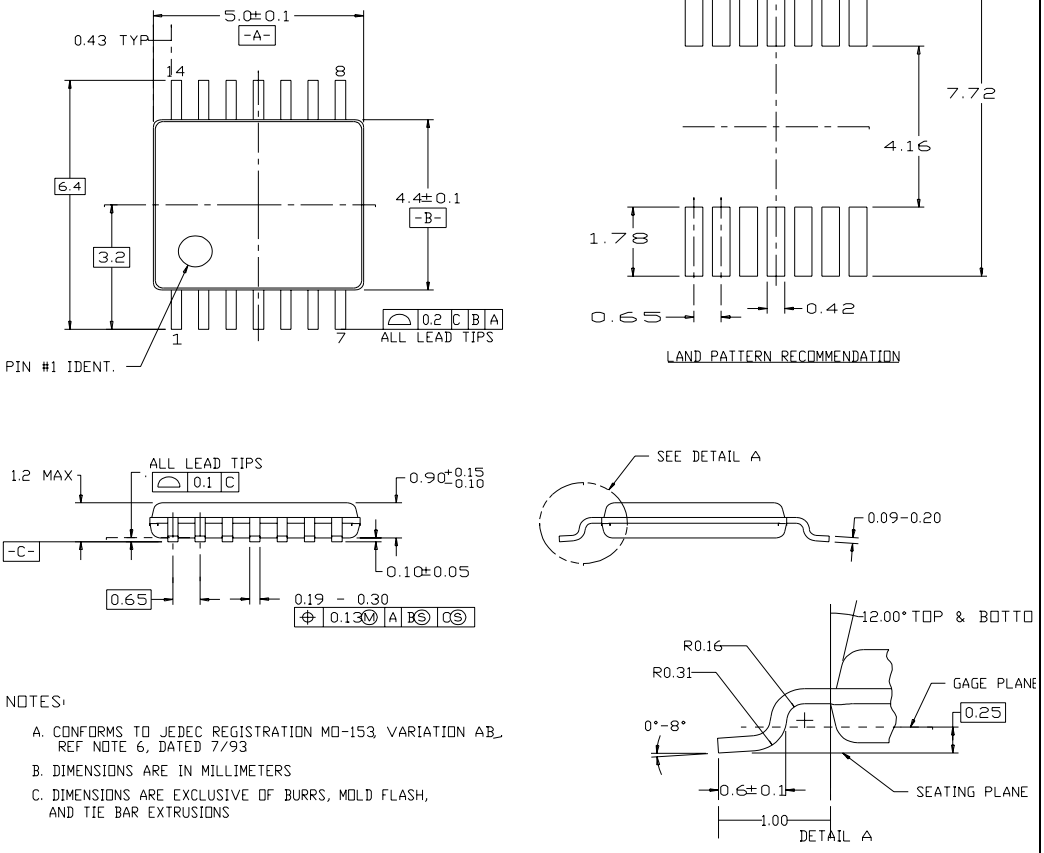
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

14LD, TSSOP, JEDEC MO-153, 4.4MM WIDE



NOTES:

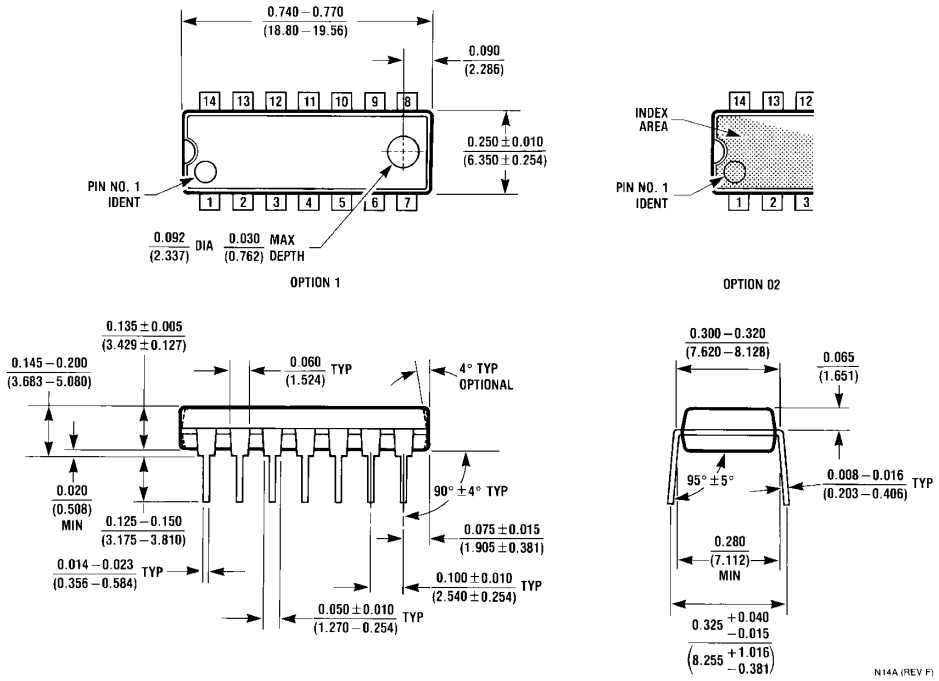
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised April 1999

74VHC4040
12-Stage Binary Counter

General Description

The VHC4040 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC4040 is a 12-stage counter which increments on the negative edge of the input clock and all outputs are reset to a low level by applying a logical high on the reset input. An input protection circuit insures that 0V to 7V can be applied to the inputs without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

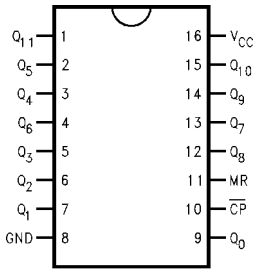
- High speed; f_{MAX} = 210 MHz at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: V_{NIH} =V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Wide operating voltage range: V_{CC} (opr) = 2V – 5.5V
- Low noise: V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC4040

Ordering Code:

Order Number	Package Number	Package Description
74VHC4040M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC4040MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4040N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

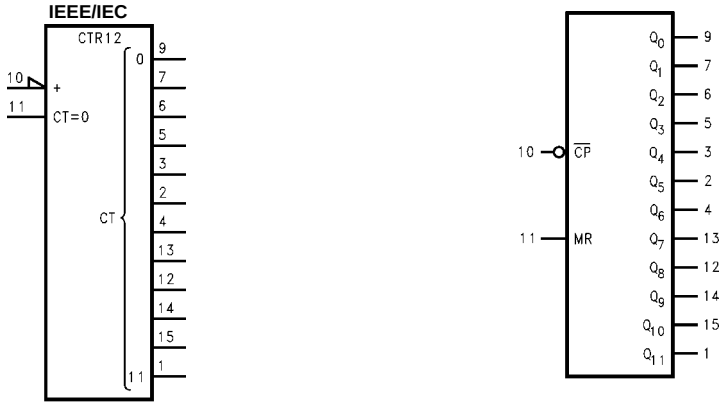
Connection Diagram



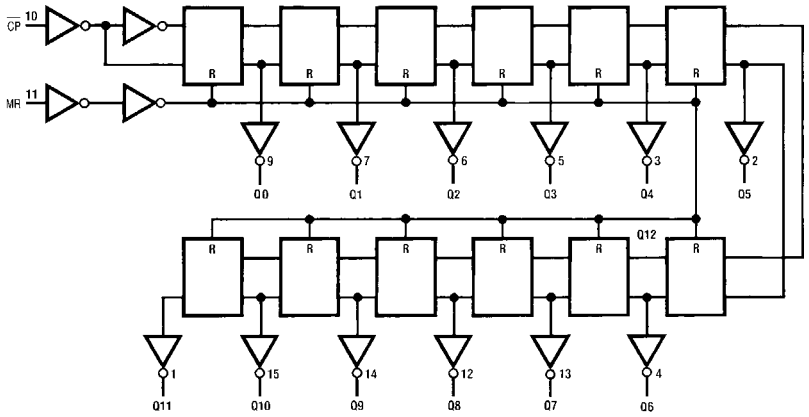
Pin Descriptions

Pin Names	Description
Q_0–Q_{11}	Flip-Flop Outputs
$\overline{CP}$	Negative Edged Triggered Clock
MR	Master Reset

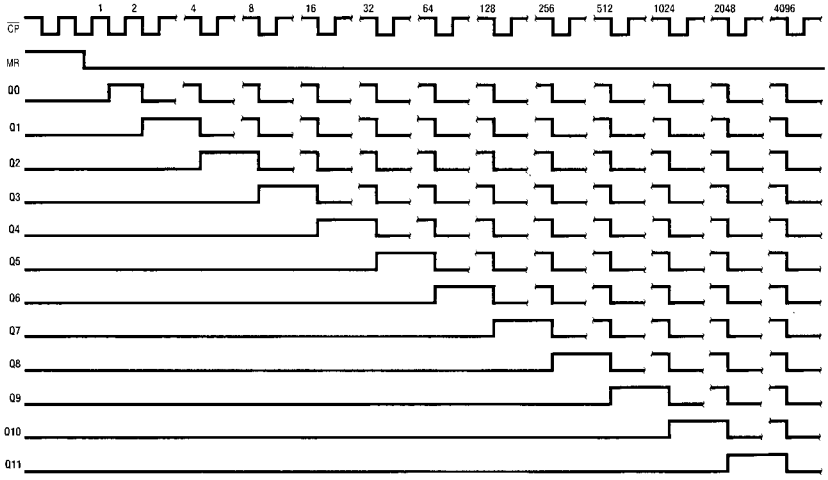
Logic Symbols



Logic Diagram



Timing Diagram



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input	2.0	1.50			1.50		V		
	Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input	2.0			0.50		0.50	V		
	Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
	Voltage	3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48				I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
	Voltage	3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44			I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

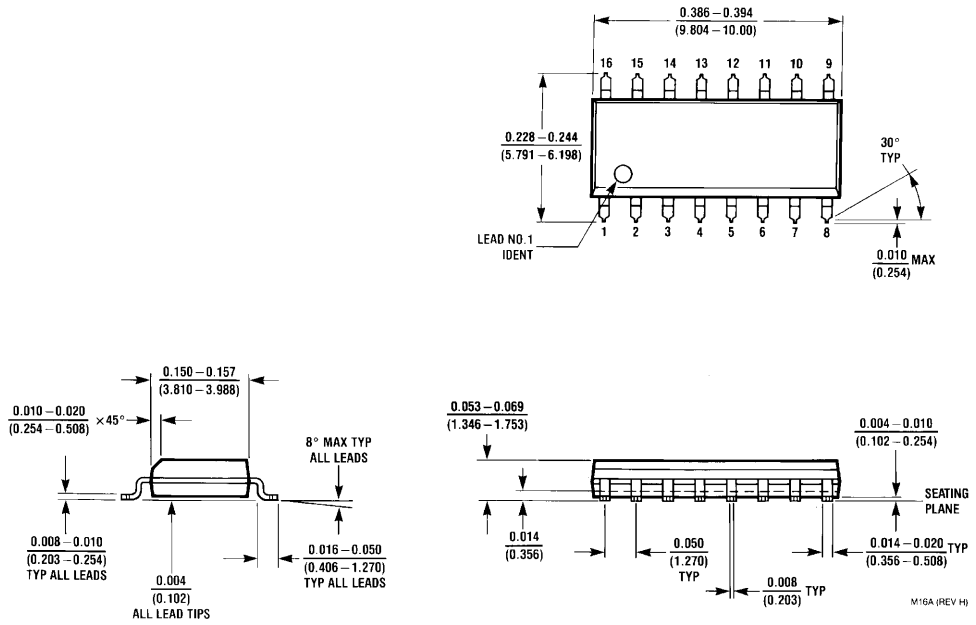
Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Time	3.3 ± 0.3		7.5	11.9	1.0	14.0	ns	C_L = 15 pF
t_{PHL}	to Q_1			10.0	15.4	1.0	17.5		C_L = 50 pF
		5.0 ± 0.5		4.8	7.3	1.0	8.5	ns	C_L = 15 pF
				6.3	9.3	1.0	10.5		C_L = 50 pF
t_{PLH}	Propagation Delay Time	3.3 ± 0.3						ns	C_L = 15 pF
t_{PHL}	between Stages from			2.4	4.4	1.0	5.0		C_L = 50 pF
	Q_n to Q_{n+1}	5.0 ± 0.5						ns	C_L = 15 pF
				1.6	3.1	1.0	3.5		C_L = 50 pF
t_{PHL}	Propagation Delay Time	3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	C_L = 15 pF
	MR–Q_n			10.8	16.3	1.0	18.5		C_L = 50 pF
		5.0 ± 0.5		5.6	8.6	1.0	10.0	ns	C_L = 15 pF
				7.1	10.6	1.0	12.0		C_L = 50 pF
f_{MAX}	Maximum Clock	3.3 ± 0.3	90	140		75		MHz	C_L = 15 pF
	Frequency		55	80		50			C_L = 50 pF
		5.0 ± 0.5	150	210		125		MHz	C_L = 15 pF
			95	125		80			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			21				pF	(Note 3)

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr) = C_{PD} * V_{CC} * f_N + I_{CC}.

AC Operating Requirements

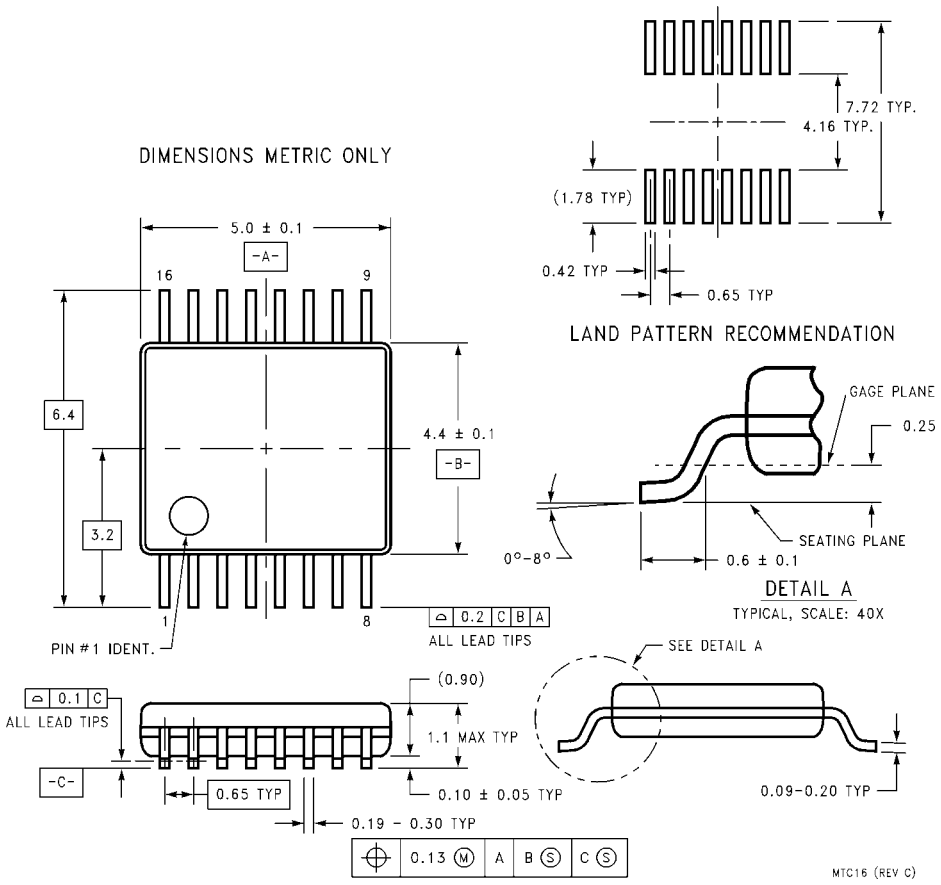
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$	Units
			Typ	Guaranteed Minimum	
t_w(L)	Minimum Pulse Width	3.3 ± 0.3		5.0	5.0	ns
t_w(H)	($\overline{CP}$)	5.0 ± 0.5		5.0	5.0	
t_w(L)	Minimum Pulse Width	3.3 ± 0.3		5.0	5.0	ns
	(MR)	5.0 ± 0.5		5.0	5.0	
t_{REC}	Minimum Removal Time	3.3 ± 0.3		5.0	5.0	ns
	(MR)	5.0 ± 0.5		5.0	5.0	

Physical Dimensions inches (millimeters) unless otherwise noted



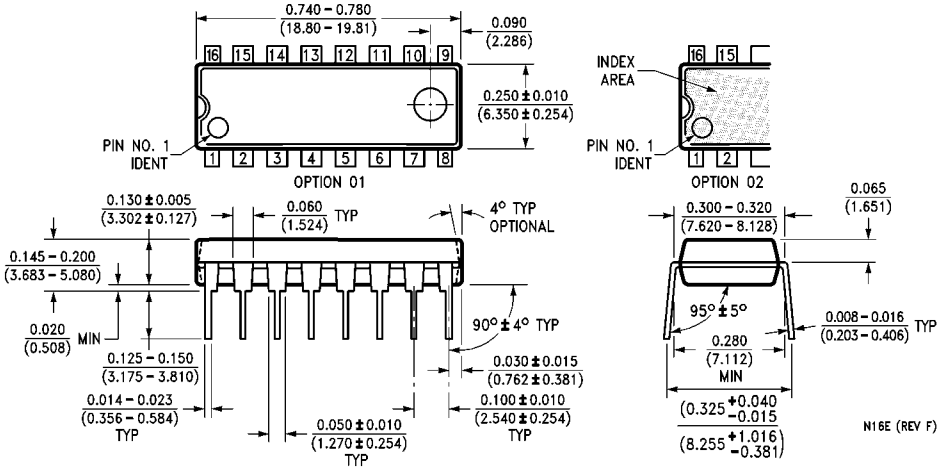
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

April 1994
Revised April 1999

74VHC4046
CMOS Phase Lock Loop

General Description

The VHC4046 is a low power phase lock loop utilizing advanced silicon-gate CMOS technology to obtain high frequency operation both in the phase comparator and VCO sections. This device contains a low power linear voltage controlled oscillator (VCO), a source follower, and three phase comparators. The three phase comparators have a common signal input and a common comparator input. The signal input has a self biasing amplifier allowing signals to be either capacitively coupled to the phase comparators with a small signal or directly coupled with standard input logic levels. This device is similar to the CD4046 except that the Zener diode of the metal gate CMOS device has been replaced with a third phase comparator.

Phase Comparator I is an exclusive OR (XOR) gate. It provides a digital error signal that maintains a 90 phase shift between the VCO's center frequency and the input signal (50% duty cycle input waveforms). This phase detector is more susceptible to locking onto harmonics of the input frequency than phase comparator I, but provides better noise rejection.

Phase comparator III is an SR flip-flop gate. It can be used to provide the phase comparator functions and is similar to the first comparator in performance.

Phase comparator II is an edge sensitive digital sequential network. Two signal outputs are provided, a comparator output and a phase pulse output. The comparator output is a 3-STATE output that provides a signal that locks the VCO output signal to the input signal with 0 phase shift between them. This comparator is more susceptible to noise throwing the loop out of lock, but is less likely to lock onto harmonics than the other two comparators.

In a typical application any one of the three comparators feed an external filter network which in turn feeds the VCO input. This input is a very high impedance CMOS input which also drives the source follower. The VCO's operating frequency is set by three external components connected to the $C1_A$, $C1_B$, R_1 and R_2 pins. An inhibit pin is provided to disable the VCO and the source follower, providing a method of putting the IC in a low power state.

The source follower is a MOS transistor whose gate is connected to the VCO input and whose drain connects the Demodulator output. This output normally is used by tying a resistor from pin 10 to ground, and provides a means of looking at the VCO input without loading down modifying the characteristics of the PLL filter.

Features

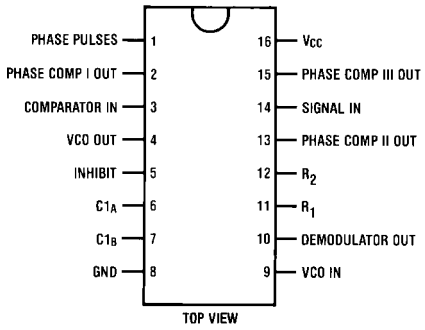
- Low dynamic power consumption: (V_{CC} = 4.5V)
- Maximum VCO operating frequency: 12 MHz (V_{CC} = 4.5V)
- Fast comparator response time (V_{CC} = 4.5V)
  - Comparator I: 25 ns
  - Comparator II: 30 ns
  - Comparator III: 25 ns
- VCO has high linearity and high temperature stability
- Pin and function compatible with the 74HC4046

Ordering Code:

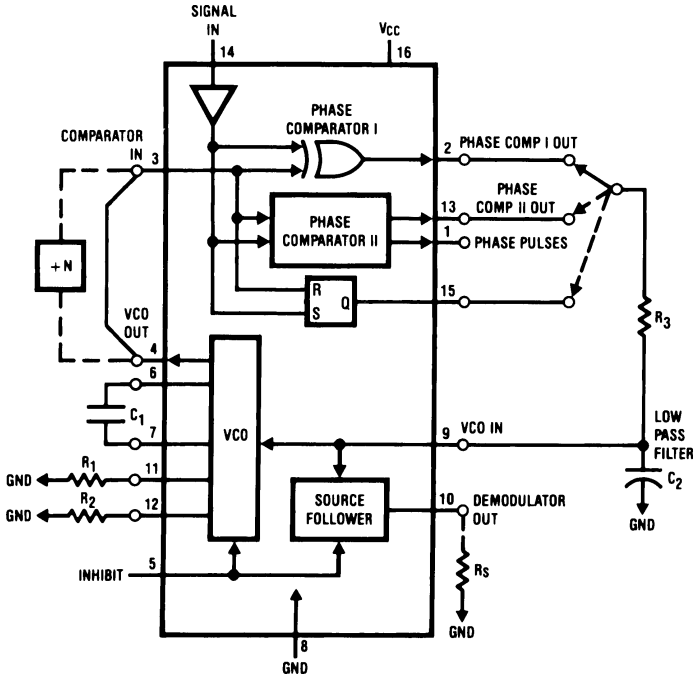
Order Number	Package Number	Package Description
74VHC4046M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC4046MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4046N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Block Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to + 7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} + 0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

		Min	Max	Units
Supply Voltage (V_{CC})		2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})		0	V_{CC}	V
Operating Temperature Range (T_A)		−40	+85	°C
Input Rise or Fall Times				
(t_r, t_f)	V_{CC} = 2.0V		1000	ns
	V_{CC} = 4.5V		500	ns
	V_{CC} = 6.0V		400	ns

Note 1: Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A=25°C		T_A=−40 to 85°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	V
			4.5V		3.15	3.15	V
			6.0V		4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	V
			4.5V		1.35	1.35	V
			6.0V		1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\| \le 20$ µA	2.0V	2.0	1.9	1.9	V
			4.5V	4.5	4.4	4.4	V
			6.0V	6.0	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL}					
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	4.2	3.98	3.84	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	5.7	5.48	5.34	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\| \le 20$ µA	2.0V	0	0.1	0.1	V
			4.5V	0	0.1	0.1	V
			6.0V	0	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL}					
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	0.2	0.26	0.33	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	0.2	0.26	0.33	V
I_{IN}	Maximum Input Current (Pins 3,5,9)	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	µA
I_{IN}	Maximum Input Current (Pin 14)	V_{IN} = V_{CC} or GND	6.0V	20	50	80	µA
I_{OZ}	Maximum 3-STATE Output Leakage Current (Pin 13)	V_{OUT} = V_{CC} or GND	6.0V		±0.25	±2.5	µA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 µA	6.0V	30	40	65	µA
		V_{IN} = V_{CC} or GND Pin 14 Open	6.0V	600	750	1200	µA

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for VHC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

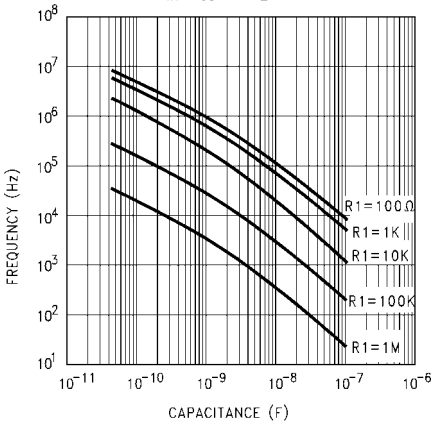
AC Electrical Characteristics

V_{CC} = 2.0 to 6.0V, CL = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified.)

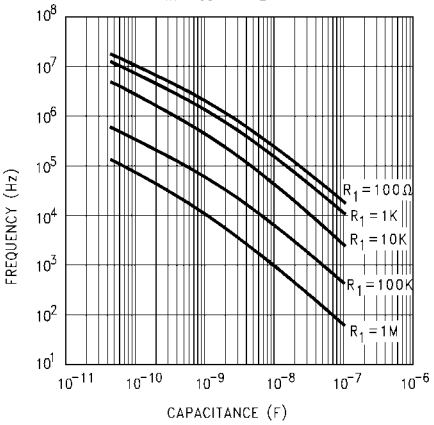
Symbol	Parameters	Conditions	V_{CC}	T_A=25C		T_A=−40 to 85°C	Units
				Typ	Guaranteed Limits		
	AC Coupled	C (series) = 100 pF	2.0V	25	100	150	mV
	Input Sensitivity,	f_{IN} = 500 kHz	4.5V	50	150	200	mV
	Signal In		6.0V	135	250	300	mV
t_r, t_f	Maximum Output		2.0V	30	75	95	ns
	Rise and Fall Time		4.5V	9	15	19	ns
			6.0V	8	12	15	ns
C_{IN}	Maximum Input		7				pF
	Capacitance						
Phase Comparator I							
t_{PHL}, t_{PLH}	Maximum Propagation		3.3V	65	117	146	ns
	Delay		4.5V	25	40	50	ns
			6.0V	20	34	43	ns
Phase Comparator II							
t_{PZL}	Maximum 3-STATE		3.3V	75	130	160	ns
	Enable Time		4.5V	25	45	56	ns
			6.0V	22	38	48	ns
t_{PZH}, t_{PHZ}	Maximum 3-STATE		3.3V	88	140	175	ns
	Enable Time		4.5V	30	48	60	ns
			6.0V	25	41	51	ns
t_{PLZ}	Maximum 3-STATE		3.3V	90	140	175	ns
	Disable Time		4.5V	32	48	60	ns
			6.0V	28	41	51	ns
t_{PHL}, t_{PLH}	Maximum Propagation		3.3V	100	146	180	ns
	Delay HIGH-to-LOW		4.5V	34	50	63	ns
	to Phase Pulses		6.0V	27	43	53	ns
Phase Comparator III							
t_{PHL}, t_{PLH}	Maximum Propagation		3.3V	75	117	146	ns
	Delay		4.5V	25	40	50	ns
			6.0V	22	34	43	ns
C_{PD}	Maximum Power	All Comparators		130			pF
	Dissipation	$V_{IN} = V_{CC}$ and GND					
	Capacitance						
Voltage Controlled Oscillator (Specified to operate from V_{CC} = 3.0V to 6.0V)							
f_{MAX}	Maximum	C_1 = 50 pF					
	Operating	R_1 = 100Ω	4.5V	7	4.5		MHz
	Frequency	$R_2 = \infty$	6.0V	11	7		MHz
		$VCO_{in} = V_{CC}$					
		C_1 = 0 pF	4.5V	12			MHz
		R_1 = 100Ω	6.0	14			MHz
		$VCO_{in} = V_{CC}$					
	Duty Cycle			50			%
Demodulator Output							
	Offset Voltage	R_S = 20 kΩ	4.5V	0.75	1.3	1.5	V
	VCO_{in}–V_{dem}						
	Offset	R_S = 20 kΩ	4.5V				
	Variation	VCO_{in} = 1.75V		0.65			V
		2.25V		0.1			
		2.75V		0.75			

Typical Performance Characteristics

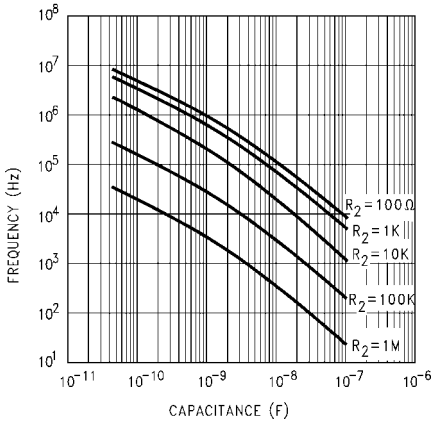
Typical Center Frequency
vs R_1, C_1 V_{CC} = 4.5V
$VCO_{IN} = V_{CC}/2$ R_2=OPEN



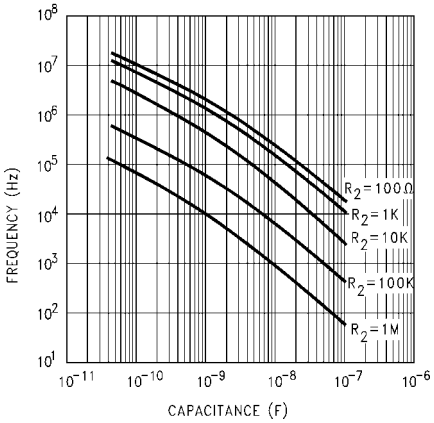
Typical Center Frequency
vs R_1, C_1 V_{CC} = 6V
$VCO_{IN} = V_{CC}/2$ R_2=OPEN



Typical Offset Frequency
vs R_2, C_1 V_{CC} = 4.5V
T=25°C VCO_{IN}=GND R_1=OPEN

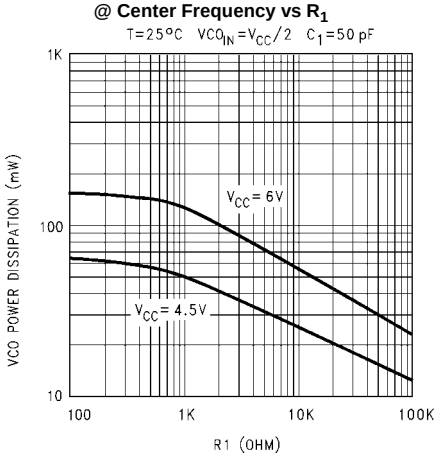


Typical Offset Frequency
vs R_2, C_1 V_{CC} = 6V
T=25°C VCO_{IN}=GND R_1=OPEN

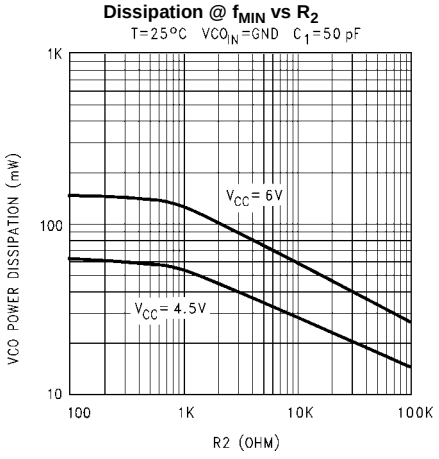


Typical Performance Characteristics (Continued)

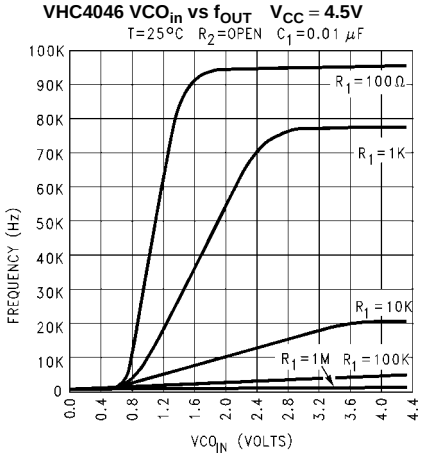
VHC4046 Typical VCO Power Dissipation @ Center Frequency vs R_1



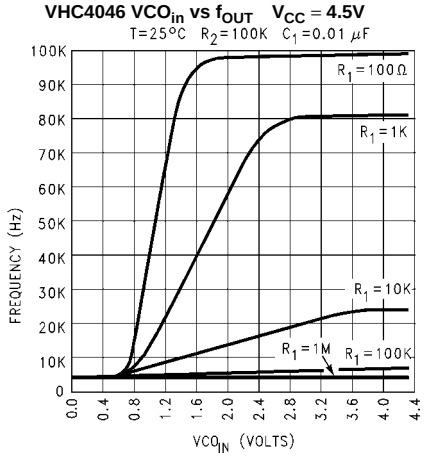
VHC4046 Typical VCO Power Dissipation @ f_{MIN} vs R_2



VHC4046 VCO_{in} vs f_{OUT} V_{CC} = 4.5V



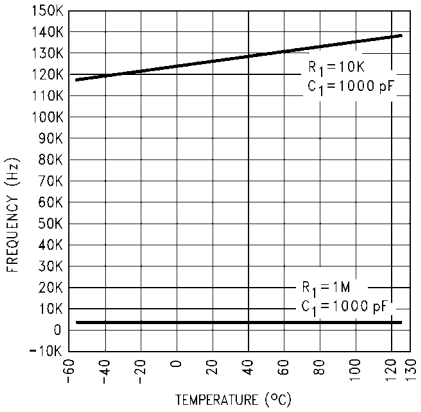
VHC4046 VCO_{in} vs f_{OUT} V_{CC} = 4.5V



Typical Performance Characteristics (Continued)

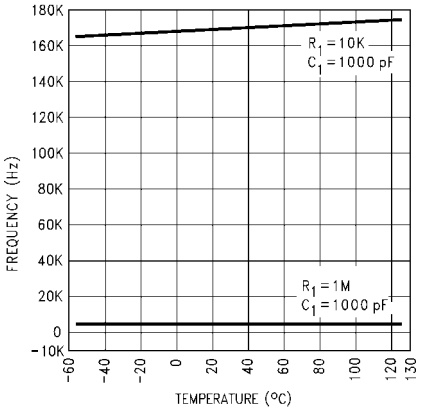
VHC4046 VCO_{out} vs Temperature $V_{CC} = 4.5V$

R_2=OPEN $VCO_{IN} = V_{CC}/2$



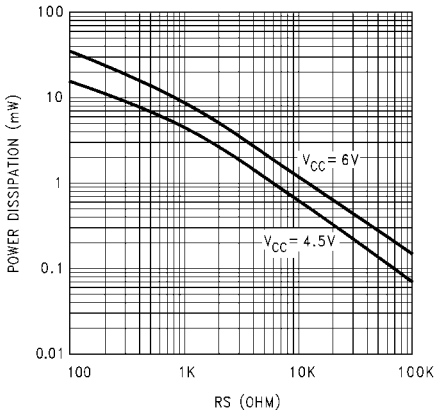
VHC4046 VCO_{out} vs Temperature $V_{CC} = 6V$

R_2=OPEN $VCO_{IN} = V_{CC}/2$



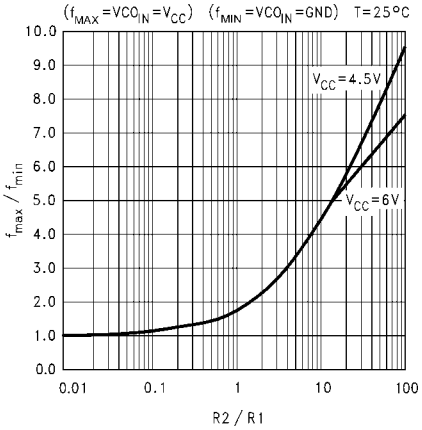
VHC4046 Typical Source Follower Power Dissipation vs RS

$VCO_{IN} = V_{CC}/2$ $R_1 = R_2$=OPEN T=25°C V_{CC}=4.5V AND 6V



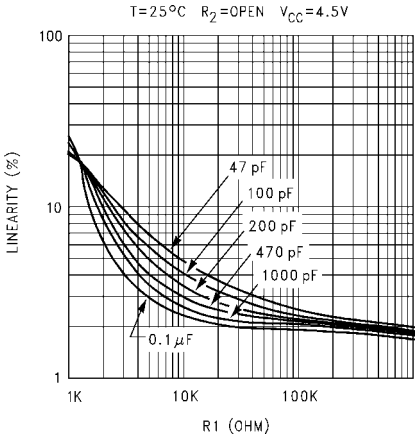
Typical f_{MAX}/f_{MIN} vs R_2/R_1 $V_{CC} = 4.5V$ & 6V f_{MAX}/f_{MIN}

(f_{MAX} = VCO_{IN} = V_{CC}) (f_{MIN} = VCO_{IN} = GND) T=25°C

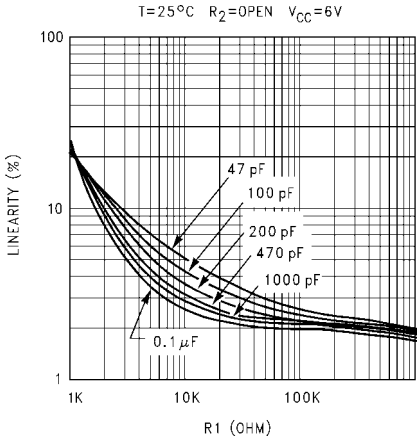


Typical Performance Characteristics (Continued)

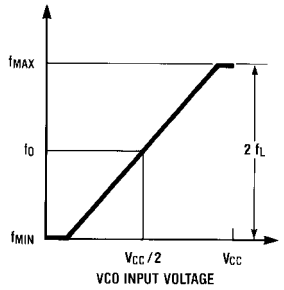
VHC4046 Typical VCO Linearity vs R_1 & C_1



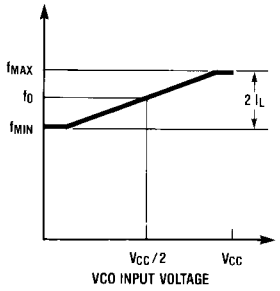
VHC4046 Typical VCO Linearity vs R_1 & C_1



VCO WITHOUT OFFSET
$R_2 = \infty$



VCO WITH OFFSET



Comparator I		Comparator II & III	
$R_2=\infty$	$R_2\neq\infty$	$R_2=\infty$	$R_2\neq\infty$
–Given: f_O –Use f_O with curve titled center frequency vs R_1, C to determine R_1 and C_1	–Given: f_O and f_L –Calculate f_{MIN} from the equation $f_{MIN} = f_O - f_L$ –Use f_{MIN} with curve titled offset frequency vs R_2, C to determine R_2 and C_1 –Calculate f_{MAX}/f_{MIN} from the equation $f_{MAX}/f_{MIN} = f_O + f_L/f_O - f_L$ –Use f_{MAX}/f_{MIN} with curve titled f_{MAX}/f_{MIN} vs R_2/R_1 to determine ratio R_2/R_1 to obtain R_1	–Given: f_{MAX} –Calculate f_O from the equation $f_O = f_{MAX}/2$ –Use f_O with curve titled center frequency vs R_1, C to determine R_1 and C_1	–Given: f_{MIN} and f_{MAX} –Use f_{MIN} with curve titled offset frequency vs R_2, C to determine R_2 and C_1 –Calculate f_{MAX}/f_{MIN} –Use f_{MAX}/f_{MIN} with curve titled f_{MAX}/f_{MIN} vs R_2/R_1 to determine ratio R_2/R_1 to obtain R_1

Detailed Circuit Description

VOLTAGE CONTROLLED OSCILLATOR/SOURCE FOLLOWER

The VCO requires two or three external components to operate. These are R_1, R_2, C_1. Resistor R_1 and capacitor C_1 are selected to determine the center frequency of the VCO. R_1 controls the lock range. As R1's resistance decreases the range of f_{MIN} to f_{MAX} increases. Thus the VCO's gain decreases. As C_1 is changed the offset (if used) of R_2, and the center frequency is changed. (See typical performance curves) R_2 can be used to set the offset frequency with 0V at VCO input. If R_2 is omitted the VCO range is from 0Hz. As R_2 is decreased the offset frequency is increased. The effect of R_2 is shown in the design information table and typical performance curves. By increasing the value of R_2 the lock range of the PLL is offset above 0Hz and the gain (Volts/rad.) does not change. In general, when offset is desired, R_2 and C_1 should be chosen first, and then R_1 should be chosen to obtain the proper center frequency.

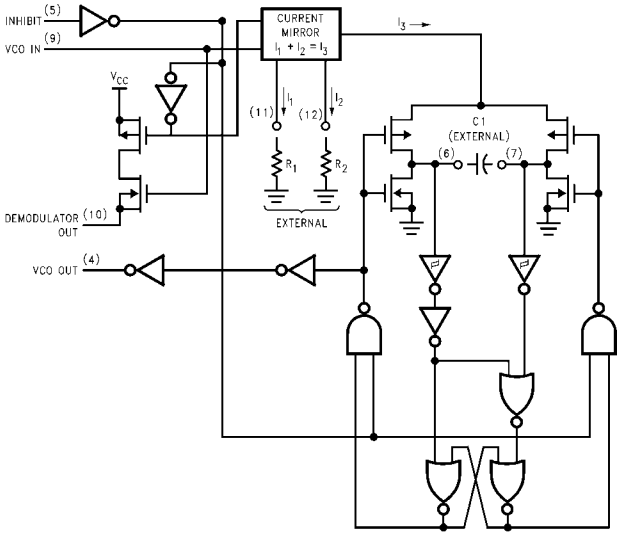


FIGURE 1. Logic Diagram for VCO

Internally the resistors set a current in a current mirror as shown in *Figure 1*. The mirrored current drives one side of the capacitor once the capacitor charges up to the threshold of the Schmitt Trigger the oscillator logic flips the capacitor over and causes the mirror to charge the opposite side of the capacitor. The output from the internal logic is then taken to pin 4.

The input to the VCO is a very high impedance CMOS input and so it will not load down the loop filter, easing the filters design. In order to make signals at the VCO input accessible without degrading the loop performance a source follower transistor is provided. This transistor can be used by connecting a resistor to ground and its drain output will follow the VCO input signal.

An inhibit signal is provided to allow disabling of the VCO and the source follower. This is useful if the internal VCO is not being used. A logic high on inhibit disables the VCO and source follower.

The output of the VCO is a standard high speed CMOS output with an equivalent LSTTL fanout of 10. The VCO output is approximately a square wave. This output can either directly feed the comparator input of the phase comparators or feed external prescalers (counters) to enable frequency synthesis.

PHASE COMPARATORS

All three phase comparators share two inputs, Signal In and Comparator In. The Signal In has a special DC bias network that enables AC coupling of input signals. If the signals are not AC coupled then this input requires logic levels the same as standard 74VHC. The Comparator input is a standard digital input. Both input structures are shown in *Figure 2*.

The outputs of these comparators are essentially standard 74VHC voltage outputs. (Comparator II is 3-STATE.)

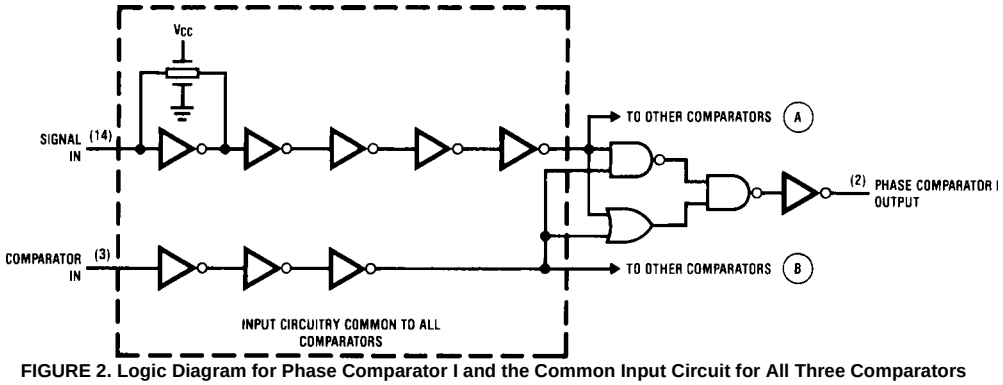


FIGURE 2. Logic Diagram for Phase Comparator I and the Common Input Circuit for All Three Comparators

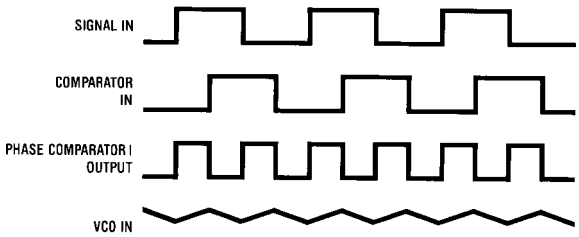


FIGURE 3. Typical Phase Comparator I. Waveforms

Thus in normal operation V_{CC} and ground voltage levels are fed to the loop filter. This differs from some phase detectors which supply a current output to the loop filter and this should be considered in the design. (The CD4046 also provides a voltage.)

Figure 4 shows the state tables for all three comparators.

PHASE COMPARATOR I

This comparator is a simple XOR gate similar to the 74HC86, and its operation is similar to an overdriven balanced modulator. To maximize lock range the input frequencies must have a 50% duty cycle. Typical input and output waveforms are shown in *Figure 3.* The output of the phase detector feeds the loop filter which averages the output voltage. The frequency range upon which the PLL will lock onto if initially out of lock is defined as the capture range. The capture range for phase detector I is dependent on the loop filter employed. The capture range can be as large as the lock range which is equal to the VCO frequency range.

To see how the detector operates refer to *Figure 3.* When two square wave inputs are applied to this comparator, an output waveform whose duty cycle is dependent on the phase difference between the two signals results. As the phase difference increases the output duty cycle increases and the voltage after the loop filter increases. Thus in order to achieve lock, when the PLL input frequency increases the VCO input voltage must increase and the phase difference between comparator in and signal in will increase. At an input frequency equal f_{MIN}, the VCO input is at 0V and this requires the phase detector output to be ground hence the two input signals must be in phase. When the input frequency is f_{MAX} then the VCO input must be V_{CC} and the phase detector inputs must be 180° out of phase.

The XOR is more susceptible to locking onto harmonics of the signal input than the digital phase detector II. This can be seen by noticing that a signal 2 times the VCO frequency results in the same output duty cycle as a signal equal the VCO frequency. The difference is that the output frequency of the 2f example is twice that of the other example. The loop filter and the VCO range should be designed to prevent locking on to harmonics.

PHASE COMPARATOR II

This detector is a digital memory network. It consists of four flip-flops and some gating logic, a three state output and a phase pulse output as shown in *Figure 5.* This comparator acts only on the positive edges of the input signals and is thus independent of signal duty cycle.

Phase comparator II operates in such a way as to force the PLL into lock with 0 phase difference between the VCO output and the signal input positive waveform edges. *Figure 6* shows some typical loop waveforms. First assume that the signal input phase is leading the comparator input. This means that the VCO's frequency must be increased to bring its leading edge into proper phase alignment. Thus the phase detector II output is set HIGH. This will cause the loop filter to charge up the VCO input increasing the VCO frequency. Once the leading edge of the comparator input is detected the output goes 3-STATE holding the VCO input at the loop filter voltage. If the VCO still lags the signal then the phase detector will again charge up to VCO input for the time between the leading edges of both waveforms.

Phase Comparator State Diagrams

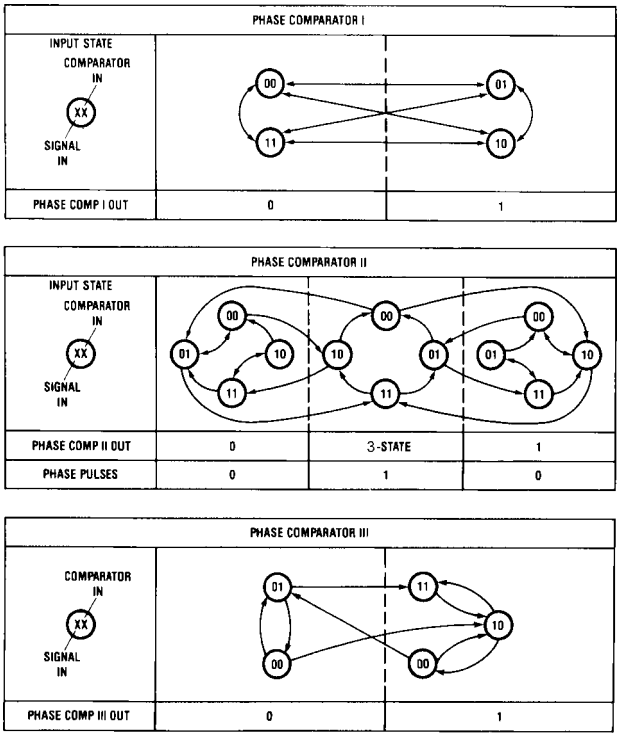


FIGURE 4. PLL State Tables

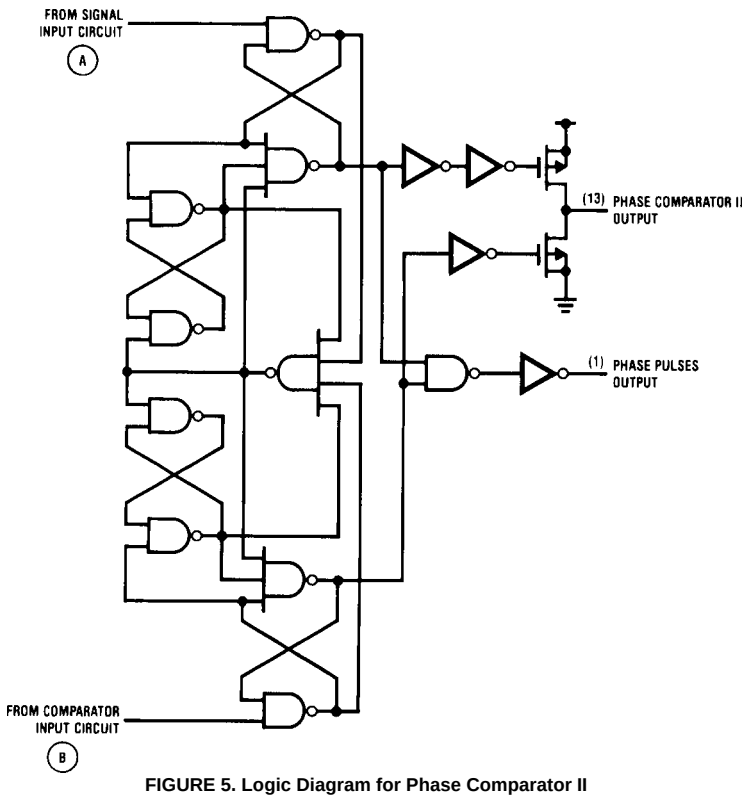


FIGURE 5. Logic Diagram for Phase Comparator II

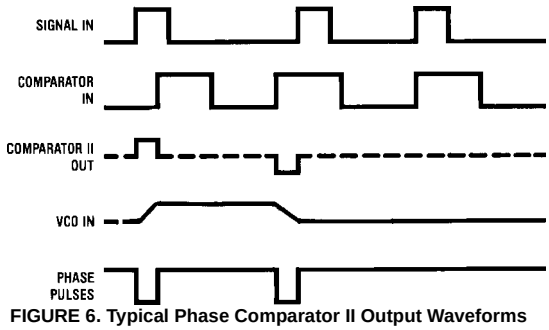


FIGURE 6. Typical Phase Comparator II Output Waveforms

If the VCO leads the signal then when the leading edge of the VCO is seen the output of the phase comparator goes LOW. This discharges the loop filter until the leading edge of the signal is detected at which time the output 3-STATEs itself again. This has the effect of slowing down the VCO to again make the rising edges of both waveform coincident.

When the PLL is out of lock the VCO will be running either slower or faster than the signal input. If it is running slower the phase detector will see more signal rising edges and so the output of the phase comparator will be high a majority of the time, raising the VCO's frequency. Conversely, if the VCO is running faster than the signal the output of the detector will be low most of the time and the VCO's output frequency will be decreased.

As one can see when the PLL is locked the output of phase comparator II will be almost always 3-STATE except for minor corrections at the leading edge of the waveforms. When the detector is 3-STATE the phase pulse output is HIGH. This output can be used to determine when the PLL is in the locked condition.

This detector has several interesting characteristics. Over the entire VCO frequency range there is no phase difference between the comparator input and the signal input. The lock range of the PLL is the same as the capture range. Minimal power is consumed in the loop filter since in lock the detector output is a high impedance. Also when no signal is present the detector will see only VCO leading edges, and so the comparator output will stay low forcing the VCO to f_{MIN} operating frequency.

Phase comparator II is more susceptible to noise causing the phase lock loop to unlock. If a noise pulse is seen on the signal input, the comparator treats it as another positive edge of the signal and will cause the output to go HIGH until the VCO leading edge is seen, potentially for a whole signal input period. This would cause the VCO to speed up during that time. When using the phase comparator I the output of that phase detector would be disturbed for only the short duration of the noise spike and would cause less upset.

PHASE COMPARATOR III

This comparator is a simple S-R Flip-Flop which can function as a phase comparator *Figure 7*. It has some similar characteristics to the edge sensitive comparator. To see how this detector works assume input pulses are applied to the signal and comparator inputs as shown in *Figure 8*. When the signal input leads the comparator input the flop is set. This will charge up the loop filter and cause the VCO to speed up, bringing the comparator into phase with the signal input. When using short pulses as input this comparator behaves very similar to the second comparator. But one can see that if the signal input is a long pulse, the output of the comparator will be forced to a one no matter how many comparator input pulses are received. Also if the VCO input is a square wave (as it is) and the signal input is pulse then the VCO will force the comparator output LOW much of the time. Therefore it is ideal to condition the signal and comparator input to short pulses. This is most easily done by using a series capacitor.

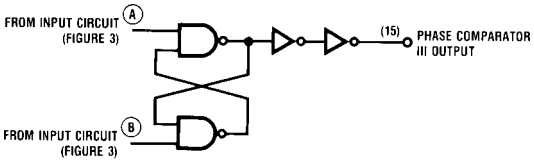


FIGURE 7. Phase Comparator III Logic Diagram

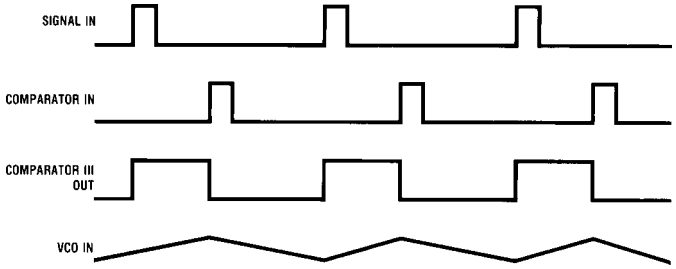
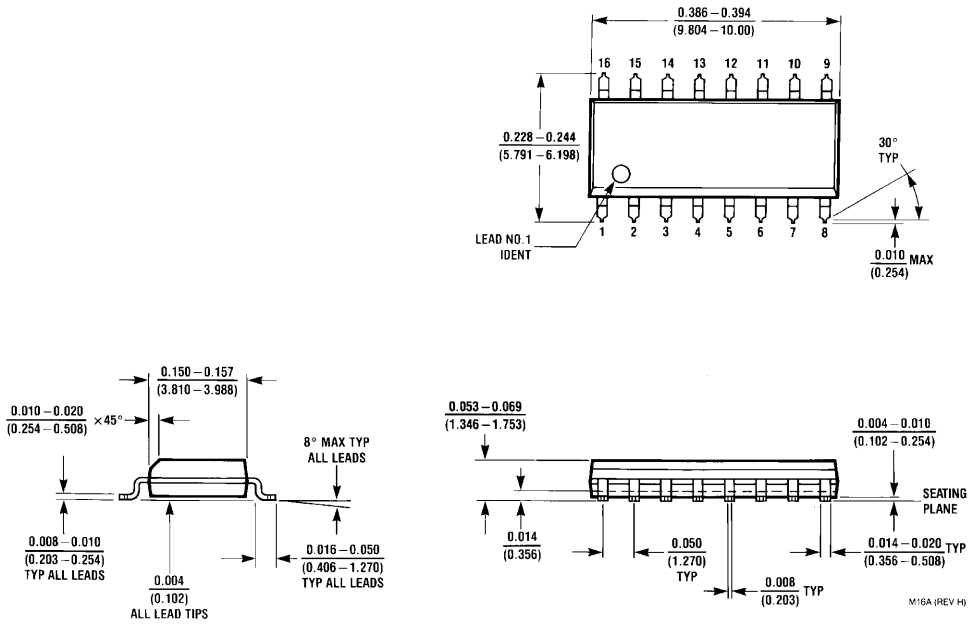


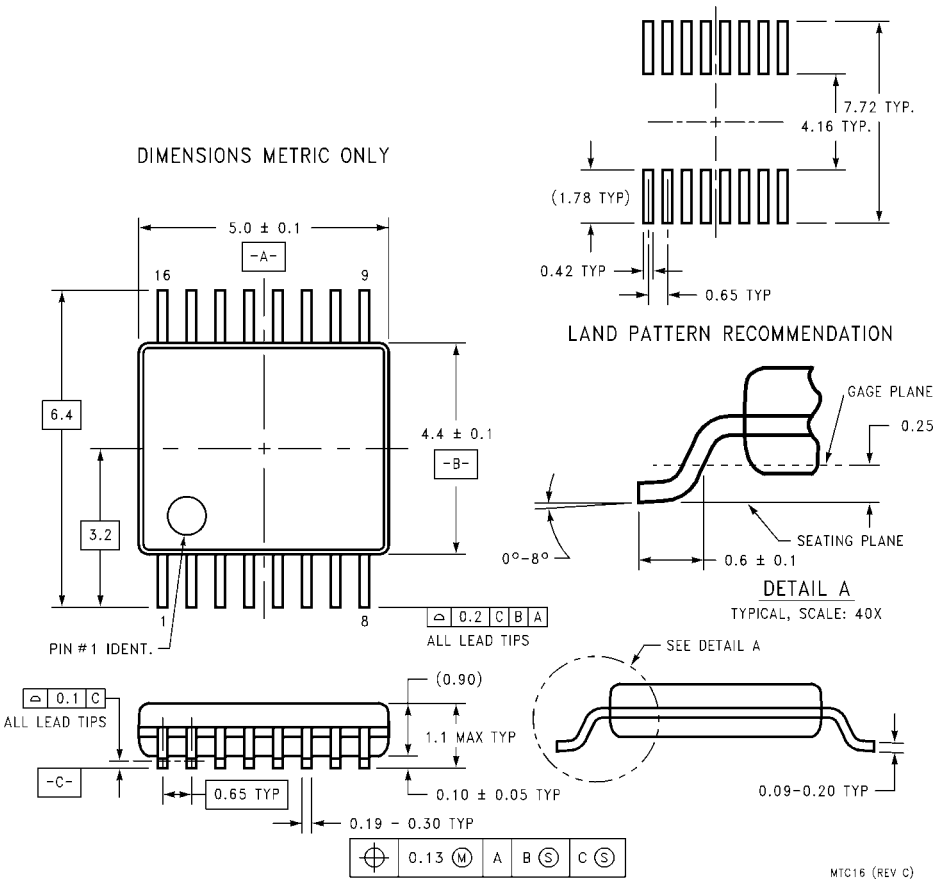
FIGURE 8. Typical Waveforms for Phase Comparator III

Physical Dimensions inches (millimeters) unless otherwise noted



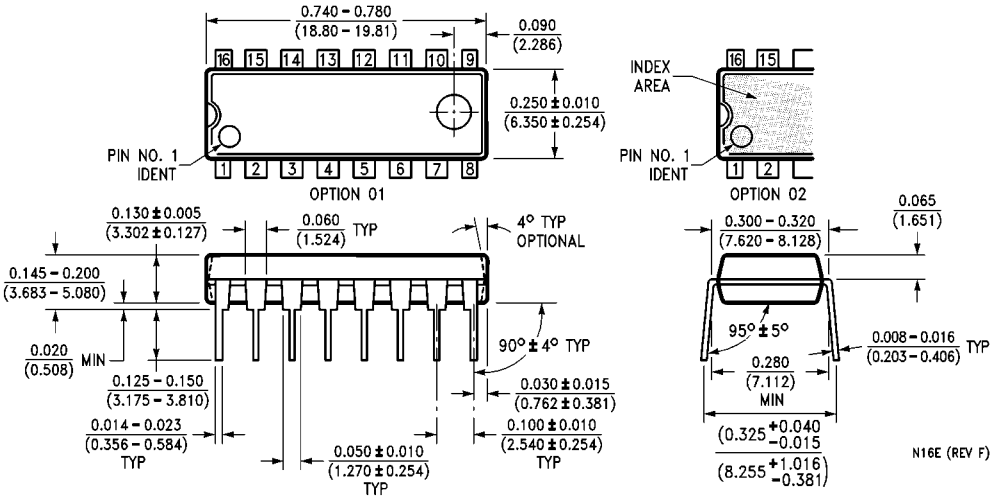
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

April 1994
Revised April 1999

74VHC4051 • 74VHC4052 • 74VHC4053
8-Channel Analog Multiplexer • Dual 4-Channel Analog Multiplexer • Triple 2-Channel Analog Multiplexer

General Description

These multiplexers are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Also these switches contain linearization circuitry which lowers the "on" resistance and increases switch linearity. These devices allow control of up to ±6V (peak) analog signals with digital control signals of 0 to 6V. Three supply pins are provided for V_{CC}, ground, and V_{EE}. This enables the connection of 0–5V logic signals when V_{CC} = 5V and an analog input range of ±5V when V_{EE} = 5V. All three devices also have an inhibit control which when high will disable all switches to their off state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to V_{CC} and ground.

VHC4051: This device connects together the outputs of 8 switches, thus achieving an 8 channel Multiplexer. The binary code placed on the A, B, and C select lines determines which one of the eight switches is "on", and connects one of the eight inputs to the common output.

VHC4052: This device connects together the outputs of 4 switches in two sets, thus achieving a pair of 4-channel multiplexers. The binary code placed on the A, and B select lines determine which switch in each 4 channel section is "on", connecting one of the four inputs in each section to its common output. This enables the implementation of a 4-channel differential multiplexer.

VHC4053: This device contains 6 switches whose outputs are connected together in pairs, thus implementing a triple 2 channel multiplexer, or the equivalent of 3 single-pole-double throw configurations. Each of the A, B, or C select lines independently controls one pair of switches, selecting one of the two switches to be "on".

Features

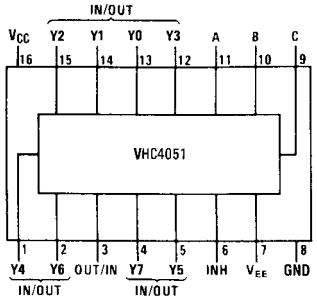
- Wide analog input voltage range: ±6V
- Low "on" resistance: 50 typ. (V_{CC}–V_{EE} = 4.5V)
  30 typ. (V_{CC}–V_{EE} = 9V)
- Logic level translation to enable 5V logic with ±5V analog signals
- Low quiescent current: 80 μA maximum
- Matched switch characteristic
- Pin and function compatible with the 74HC4051/ 4052/ 4053

Ordering Code:

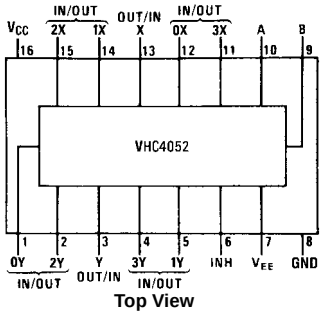
Order Number	Package Number	Package Description
74VHC4051M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC4051WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC4051MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4051N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74VHC4052M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC4052WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC4052MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4052N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74VHC4053M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC4053WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC4053MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4053N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

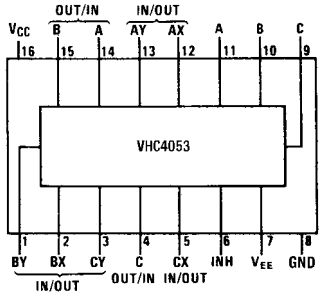
Connection Diagrams



Top View



Top View



Top View

Truth Tables

4051

Input				"ON"
INH	C	B	A	Channel
H	X	X	X	None
L	L	L	L	Y0
L	L	L	H	Y1
L	L	H	L	Y2
L	L	H	H	Y3
L	H	L	L	Y4
L	H	L	H	Y5
L	H	H	L	Y6
L	H	H	H	Y7

4052

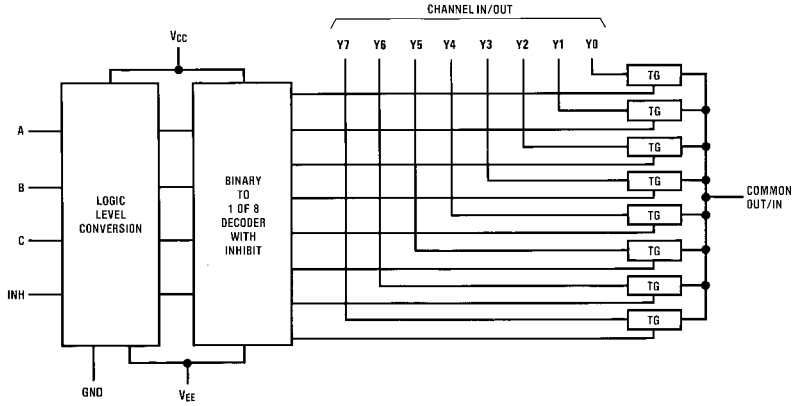
Inputs			"ON" Channels	
INH	B	A	X	Y
H	X	X	None	None
L	L	L	0X	0Y
L	L	H	1X	1Y
L	H	L	2X	2Y
L	H	H	3X	3Y

4053

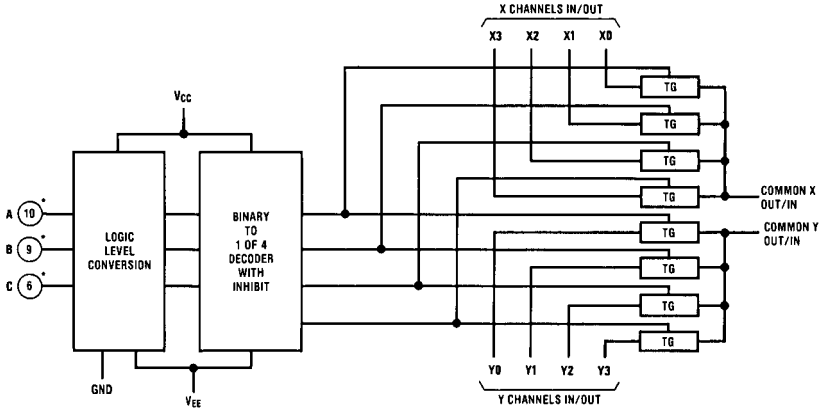
Input				"ON" Channels		
INH	C	B	A	C	B	A
H	X	X	X	None	None	None
L	L	L	L	CX	BX	AX
L	L	L	H	CX	BX	AY
L	L	H	L	CX	BY	AX
L	L	H	H	CX	BY	AY
L	H	L	L	CY	BX	AX
L	H	L	H	CY	BX	AY
L	H	H	L	CY	BY	AX
L	H	H	H	CY	BY	AY

Logic Diagrams

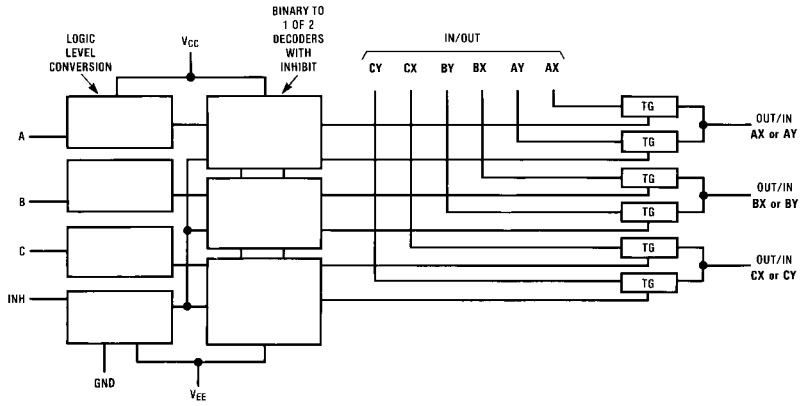
74VHC4051



74VHC4052



74VHC4053



Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.5V
Supply Voltage (V_{EE})	+0.5 to −7.5V
Control Input Voltage (V_{IN})	−1.5 to V_{CC}+1.5V
Switch I/O Voltage (V_{IO})	V_{EE}−0.5 to V_{CC}+0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
Output Current, per pin (I_{OUT})	±25 mA
V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
Supply Voltage (V_{EE})	0	−6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times (t_r, t_f)			
V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter		Conditions	V_{EE}	V_{CC}		$T_A = 25°C$	$T_A = -40$ to $85°C$	Units
						Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level				2.0V		1.5	1.5	V
	Input Voltage				4.5V		3.15	3.15	V
					6.0V		4.2	4.2	V
V_{IL}	Maximum LOW Level				2.0V		0.5	0.5	V
	Input Voltage				4.5V		1.35	1.35	V
					6.0V		1.8	1.8	V
R_{ON}	Maximum "ON" Resistance		$V_{INH} = V_{IL}$, $I_S = 2.0$ mA	GND	4.5V	40	160	200	Ω
	(Note 5)		$V_{IS} = V_{CC}$ to V_{EE}	−4.5V	4.5V	30	120	150	Ω
			(Figure 1)	−6.0V	6.0V	20	100	125	Ω
			$V_{INH} = V_{IL}$, $I_S = 2.0$ mA	GND	2.0V	100	230	280	Ω
			$V_{IS} = V_{CC}$ or V_{EE}	GND	4.5V	40	110	140	Ω
			(Figure 1)	−4.5V	4.5V	20	90	120	Ω
				−6.0V	6.0V	15	80	100	Ω
R_{ON}	Maximum "ON" Resistance		$V_{INH} = V_{IL}$	GND	4.5V	10	20	25	Ω
	Matching		$V_{IS} = V_{CC}$ to GND	−4.5V	4.5V	5	10	15	Ω
				−6.0V	6.0V	5	10	12	Ω
I_N	Maximum Control		$V_{IN} = V_{CC}$ or GND				±.05	±0.5	µA
	Input Current		$V_{CC} = 2 - 6V$						
I_{CC}	Maximum Quiescent		$V_{IN} = V_{CC}$ or GND	GND	6.0V		4	40	µA
	Supply Current		$I_{OUT} = 0$ µA	−6.0V	6.0V		8	80	µA
I_{IZ}	Maximum Switch "OFF"		$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±60	±300	nA
	Leakage Current		$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±100	±500	nA
	(Switch Input)		$V_{INH} = V_{IH}$ (Figure 2)						
I_{IZ}	Maximum Switch "ON"		$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.1	±1.0	µA
	Leakage Current	VHC4051	$V_{INH} = V_{IL}$	−6.0V	6.0V		±0.2	±2.0	µA
			(Figure 3)						
			$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.050	±0.5	µA
		VHC4052	$V_{INH} = V_{IL}$	−6.0V	6.0V		±0.1	±1.0	µA
			(Figure 3)						
			$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.05	±0.5	µA
		VHC4053	$V_{INH} = V_{IL}$	−6.0V	6.0V		±0.5	±0.5	µA
			(Figure 3)						
I_{IZ}	Maximum Switch		$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±0.1	±1.0	µA
	"OFF" Leakage	VHC4051	$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±0.2	±2.0	µA
	Current (Common Pin)		$V_{INH} = V_{IH}$						
			$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±0.05	±0.5	µA
		VHC4052	$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±0.1	±1.0	µA
			$V_{INH} = V_{IH}$						
			$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±0.05	±0.5	µA
		VHC4053	$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±0.05	±0.5	µA
			$V_{INH} = V_{IH}$						

Note 4: For a power supply of 5V ±10% the worst case on resistances (R_{ON}) occurs for VHC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5$V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occur for CMOS at the higher voltage and so the 5.5V values should be used.

Note 5: At supply voltages (V_{CC}–V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

Note 6: Adjust 0 dB for f = 1 kHz (Null R1/R_{ON} Attenuation).

AC Electrical Characteristics

V_{CC} = 2.0V – 6.0V, V_{EE} = 0V – 6V, C_L = 50 pF (unless otherwise specified)

Symbol	Parameter	Conditions		V_{EE}	V_{CC}	T_A=25°C	T_A=–40 to 85°C		Units
						Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay Switch In to Out			GND	3.3V	25	35	40	ns
				GND	4.5V	5	12	15	ns
				–4.5V	4.5V	4	8	12	ns
				–6.0V	6.0V	3	7	11	ns
t_{PZL}, t_{PZH}	Maximum Switch Turn "ON" Delay	R_L = 1 kΩ		GND	3.3V	92	200	250	ns
				GND	4.5V		69	87	ns
				–4.5V	4.5V	16	46	58	ns
				–6.0V	6.0V	15	41	51	ns
t_{PHZ}, t_{PLZ}	Maximum Switch Turn "OFF" Delay			GND	3.3V	65	170	210	ns
				GND	4.5V	28	58	73	ns
				–4.5V	4.5V	18	37	46	ns
				–6.0V	6.0V	16	32	41	ns
f_{MAX}	Minimum Switch Frequency Response 20 log (V_I/V_O) = 3 dB			GND	4.5V	30			MHz
				–4.5V	4.5V	35			MHz
	Control to Switch Feedthrough Noise	R_L = 600Ω, f = 1 MHz, C_L = 50 pF	V_{IS} = 4 V_{PP}	0V	4.5V	1080			mV
			V_{IS} = 8 V_{PP}	–4.5V	4.5V	250			mV
	Crosstalk between any Two Switches	R_L = 600Ω, f = 1 MHz	V_{IS} = 4 V_{PP}	0V	4.5	–52			dB
			V_{IS} = 8 V_{PP}	–4.5V	4.5V	–50			dB
	Switch OFF Signal Feedthrough Isolation	R_L = 600Ω, f = 1 MHz, V_{CTL} = V_{IL}	V_{IS} = 4 V_{PP}	0V	4.5V	–42			dB
			V_{IS} = 8 V_{PP}	–4.5V	4.5V	–44			dB
THD	Sinewave Harmonic Distortion	R_L = 10 kΩ, C_L = 50 pF, f = 1 kHz	V_{IS} = 4 V_{PP}	0V	4.5V	0.013			%
			V_{IS} = 8 V_{PP}	–4.5V	4.5V	0.008			%
C_{IN}	Maximum Control Input Capacitance					5	10	10	pF
C_{IN}	Maximum Switch Input Capacitance	Input				15			pF
		4051 Common				90			
		4052 Common				45			
		4053 Common				30			
C_{IN}	Maximum Feedthrough Capacitance					5			pF

AC Test Circuits and Switching Time Waveforms

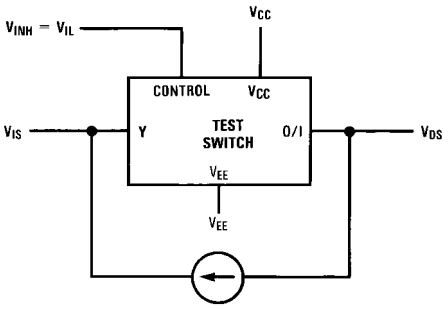


FIGURE 1. "ON" Resistance

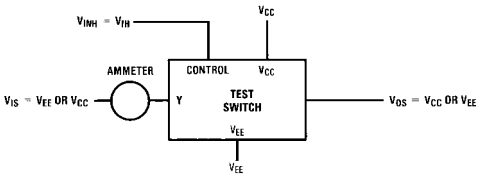


FIGURE 2. "OFF" Channel Leakage Current

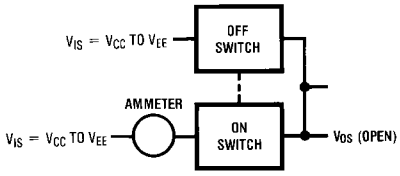
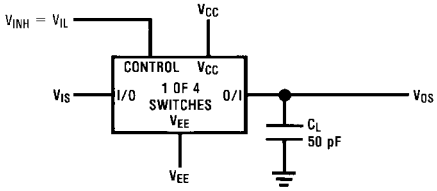


FIGURE 3. "ON" Channel Leakage Current



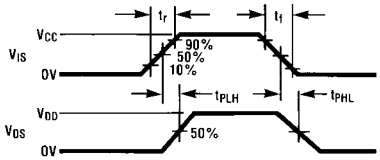
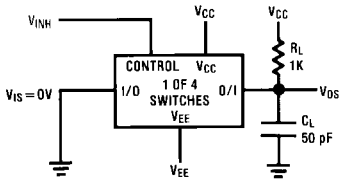


FIGURE 4. t_{PHL}, t_{PLH} Propagation Delay Time Signal Input to Signal Output



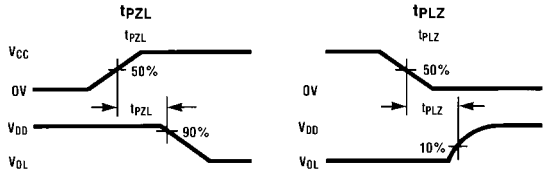
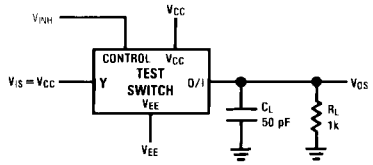


FIGURE 5. t_{PZL}, t_{PLZ} Propagation Delay Time Control to Signal Output



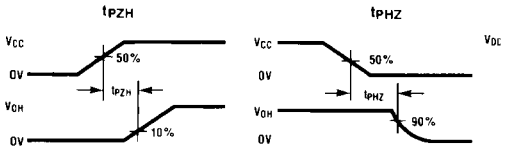
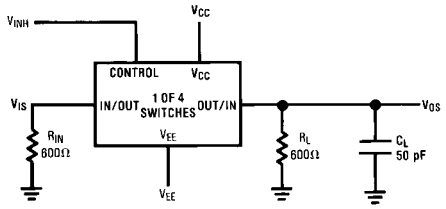


FIGURE 6. t_{PZH}, t_{PHZ} Propagation Delay TIme Control to Signal Output



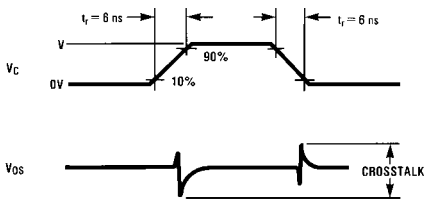


FIGURE 7. Crosstalk: Control Input to Signal Output

AC Test Circuits and Switching Time Waveforms (Continued)

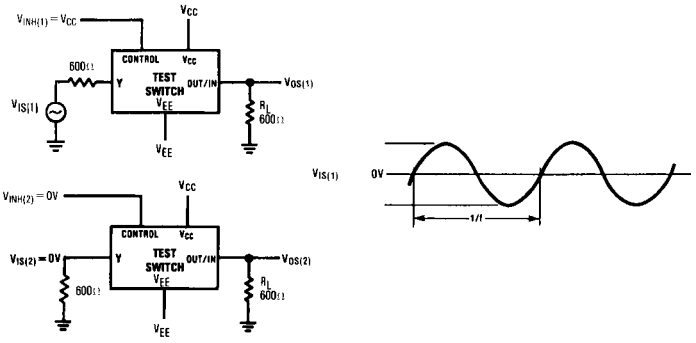
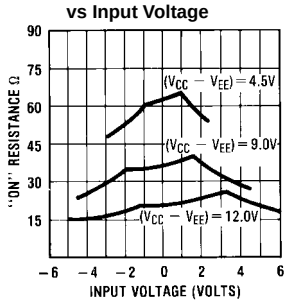


FIGURE 8. Crosstalk Between Any Two Switches

Typical Performance Characteristics

Typical "On" Resistance vs Input Voltage

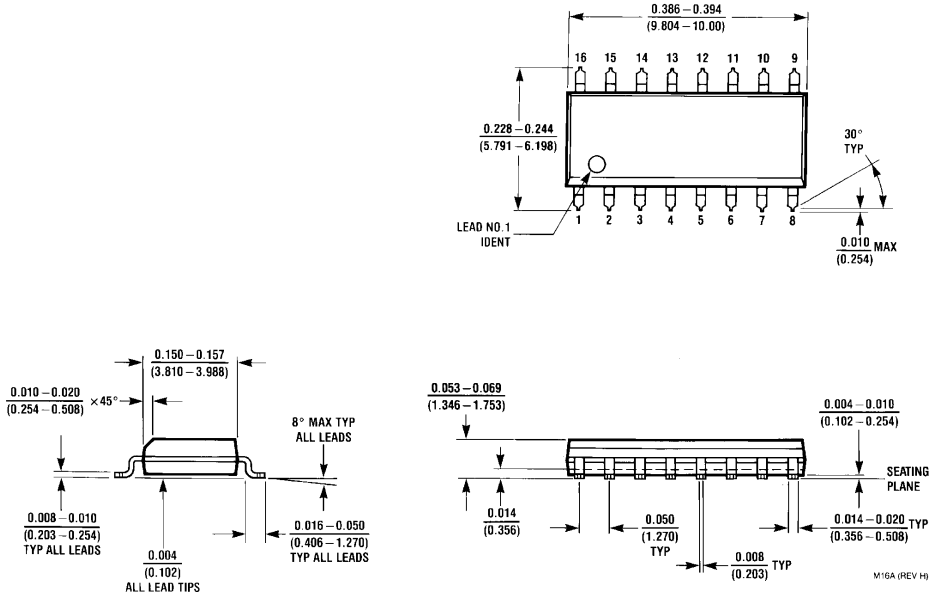


V_{CC}=−V_{EE}

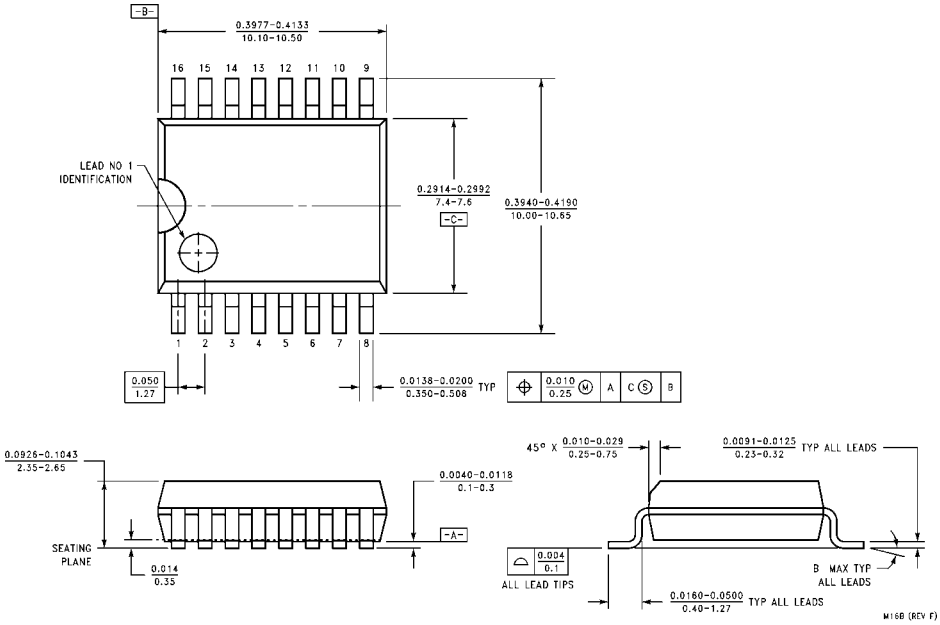
Special Considerations

In certain applications the external load-resistor current may include both V_{CC} and signal line components. To avoid drawing V_{CC} current when switch current flows into the analog switch pins, the voltage drop across the switch must not exceed 1.2V (calculated from the ON resistance).

Physical Dimensions inches (millimeters) unless otherwise noted

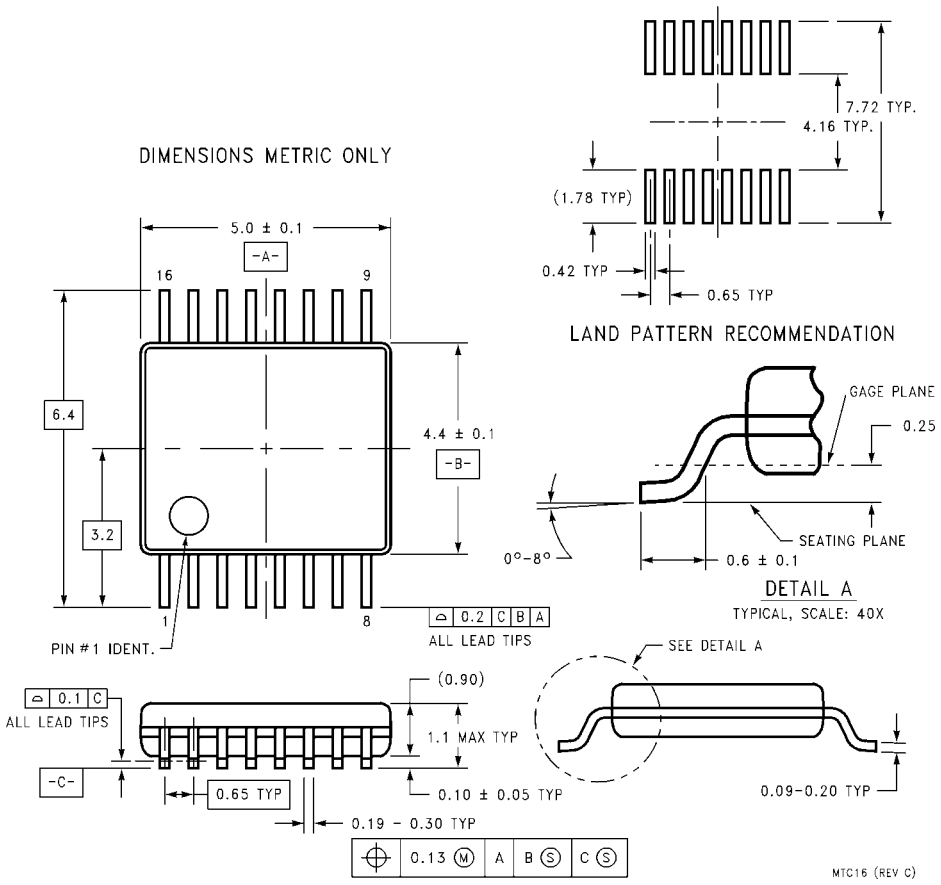


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



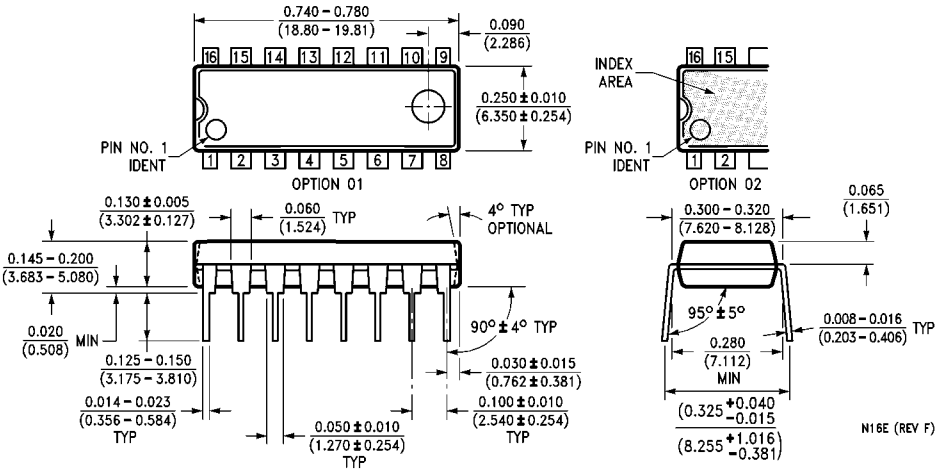
16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M16B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

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April 1994
Revised January 2000

74VHC4066
Quad Analog Switch

General Description

These devices are digitally controlled analog switches utilizing advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and visa-versa. Also the 4066 switches contain linearization circuitry which lowers the "on" resistance and increases switch linearity. The 4066 devices allow control of up to 12V (peak) analog signals with digital control signals of the same range. Each switch has its own control input which disables each switch when low. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to V_{CC} and ground.

Features

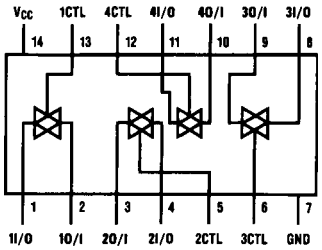
- Typical switch enable time: 15 ns
- Wide analog input voltage range: 0–12V
- Low "on" resistance: 30 typ. ('4066)
- Low quiescent current: 80 µA maximum (74VHC)
- Matched switch characteristics
- Individual switch controls
- Pin and function compatible with the 74HC4066

Ordering Code:

Order Number	Package Number	Package Description
74VHC4066M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHC4066MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4066N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

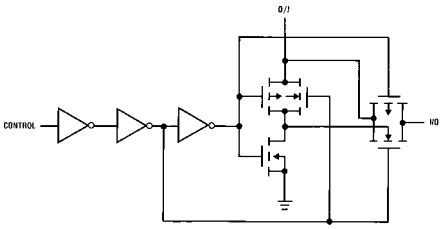
Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Top View

Schematic Diagram



Truth Table

Input	Switch
CTL	I/O–O/I
L	"OFF"
H	"ON"

Absolute Maximum Ratings (Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +15V
DC Control Input Voltage (V_{IN})	−1.5 to V_{CC} + 1.5V
DC Switch I/O Voltage (V_{IO})	V_{EE} − 0.5 to V_{CC} + 0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D) (Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	12	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times (t_r, t_f)			
V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 9.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A=25°C		T_A=−40 to 85°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	V
			4.5V		3.15	3.15	V
			9.0V		6.3	5.3	V
			12.0V		8.4	8.4	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	V
			4.5V		1.35	1.35	V
			9.0V		2.7	2.7	V
			12.0V		3.6	3.6	V
R_{ON}	Maximum "ON" Resistance See (Note 5)	V_{CTL} = V_{IH}, I_S = 2.0 mA V_{IS} = V_{CC} to GND (*Figure 1*)	4.5V	100	170	200	Ω
			9.0V	50	85	105	Ω
			12.0V	30	70	85	Ω
		V_{CTL} = V_{IH}, I_S = 2.0 mA V_{IS} = V_{CC} or GND (*Figure 1*)	2.0V	120	180	215	Ω
			4.5V	50	80	100	Ω
			9.0V	35	60	75	Ω
			12.0V	20	40	60	Ω
R_{ON}	Maximum "ON" Resistance Matching	V_{CTL} = V_{IH} V_{IS} = V_{CC} to GND	4.5V	10	15	20	Ω
			9.0V	5	10	15	Ω
			12.0V	5	10	15	Ω
I_{IN}	Maximum Control Input Current	V_{IN} = V_{CC} or GND V_{CC} = 2 − 6V			±0.05	±0.5	µA
I_{IZ}	Maximum Switch "OFF" Leakage Current	V_{OS} = V_{CC} or GND V_{IS} = GND or V_{CC} V_{CTL} = V_{IL} (*Figure 2*)	6.0V	10	±60	±600	nA
			9.0V	15	±80	±800	nA
			12.0V	20	±100	±1000	nA
I_{IZ}	Maximum Switch "ON" Leakage Current	V_{IS} = V_{CC} to GND V_{CTL} = V_{IH} V_{OS} = OPEN (*Figure 3*)	6.0V	10	±40	±150	nA
			9.0V	15	±50	±200	nA
			12.0V	20	±60	±300	nA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 µA	6.0V		1.0	10	µA
			9.0V		2.0	20	µA
			12.0V		4.0	40	µA

Note 4: For a power supply of 5V ± 10% the worst case on resistance (R_{ON}) occurs for VHC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occurs for CMOS at the higher voltage and so the 5.5V values should be used.

Note 5: At supply voltages (V_{CC} − GND) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

AC Electrical Characteristics

V_{CC} = 2.0V–6.0V V_{EE} = 0V–12V, C_L = 50 pF (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A=25°C		T_A=−40 to 85°C	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation		3.3V	25	30	20	ns
	Delay Switch In to Out		4.5V	5	10	13	ns
			9.0V	4	8	10	ns
			12.0V	3	7	11	ns
t_{PZL}, t_{PZH}	Maximum Switch Turn	R_L = 1 kΩ	3.3V	30	58	73	ns
	"ON" Delay		4.5V	12	20	25	ns
			9.0V	6	12	15	ns
			12.0V	5	10	13	ns
t_{PHZ}, t_{PLZ}	Maximum Switch Turn	R_L = 1 kΩ	3.3V	60	100	125	ns
	"OFF" Delay		4.5V	25	36	45	ns
			9.0V	20	32	40	ns
			12.0V	15	30	38	
	Minimum Frequency	R_L = 600Ω	4.5V	40			MHz
	Response (*Figure 7*)	V_{IS} = 2 V_{PP} at (V_{CC}/2)	9.0V	100			MHz
	20 log(V_O/V_I) = −3 dB	(Note 6)(Note 7)					
	Crosstalk Between	R_L = 600Ω, F = 1 MHz					
	any Two Switches	(Note 7)(Note 8)	4.5V	−52			dB
	(*Figure 8*)		9.0V	−50			dB
	Peak Control to Switch	R_L = 600Ω, F = 1 MHz	4.5V	100			mV
	Feedthrough Noise	C_L = 50 pF	9.0V	250			mV
	(*Figure 9*)						
	Switch OFF Signal	R_L = 600Ω, F = 1 MHz					
	Feedthrough	$V_{(CT)}$ V_{IL}					
	Isolation	(Note 7)(Note 8)	4.5V	−42			dB
	(*Figure 10*)		9.0V	−44			dB
THD	Total Harmonic	R_L = 10 kΩ, C_L = 50 pF,					
	Distortion	F = 1 kHz					
	(*Figure 11*)	V_{IS} = 4 V_{PP}	4.5V	.013			%
		V_{IS} = 8 V_{PP}	9.0V	.008			%
C_{IN}	Maximum Control			5	10	10	pF
	Input Capacitance						
C_{IN}	Maximum Switch			20			pF
	Input Capacitance						
C_{IN}	Maximum Feedthrough	V_{CTL} = GND		0.5			pF
	Capacitance						
C_{PD}	Power Dissipation			15			pF
	Capacitance						

Note 6: Adjust 0 dBm for F = 1 kHz (Null R_L/R_{ON} Attenuation).

Note 7: V_{IS} is centered at V_{CC}/2.

Note 8: Adjust input for 0 dBm.

AC Test Circuits and Switching Time Waveforms

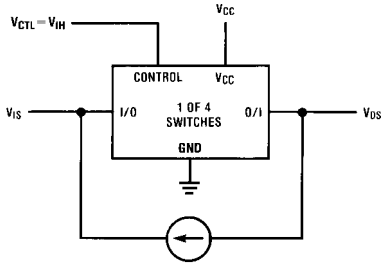


FIGURE 1. "ON" Resistance

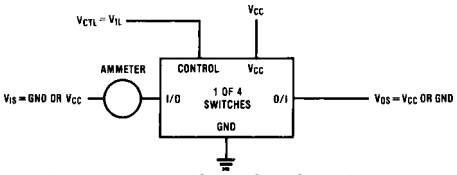


FIGURE 2. "OFF" Channel Leakage Current

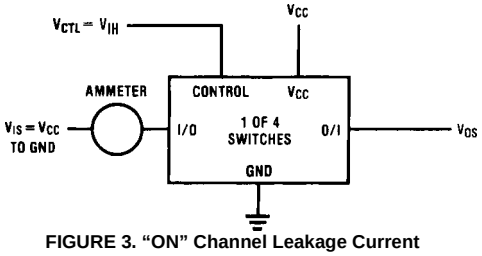


FIGURE 3. "ON" Channel Leakage Current

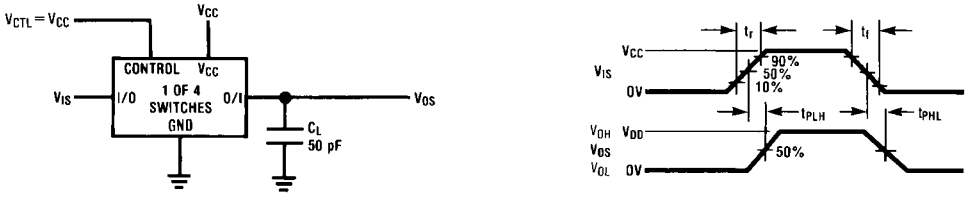


FIGURE 4. t_{PHL}, t_{PLH} Propagation Delay Time Signal Input to Signal Output

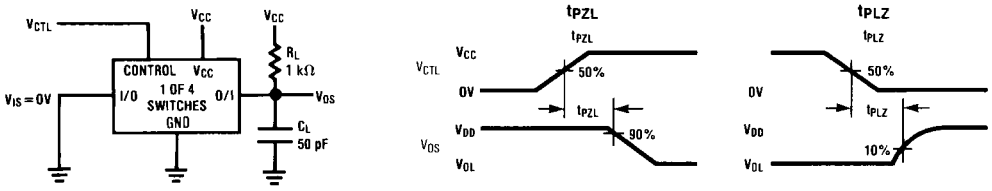


FIGURE 5. t_{PZL}, t_{PLZ} Propagation Delay Time Control to Signal Output

AC Test Circuits and Switching Time Waveforms (Continued)

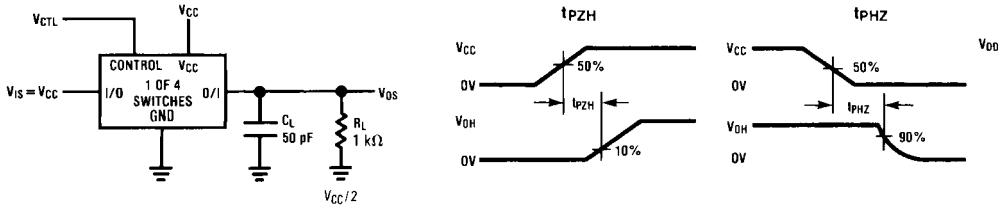


FIGURE 6. t_{PZH}, t_{PHZ} Propagation Delay Time Control to Signal Output

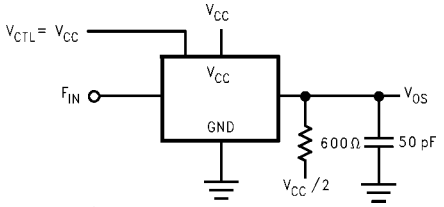


FIGURE 7. Frequency Response

Crosstalk and Distortion Test Circuits

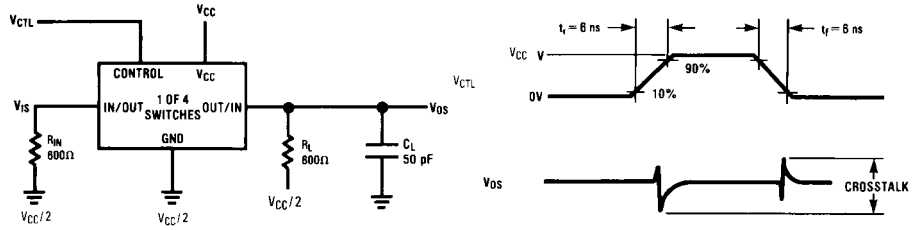


FIGURE 8. Crosstalk: Control Input to Signal Output

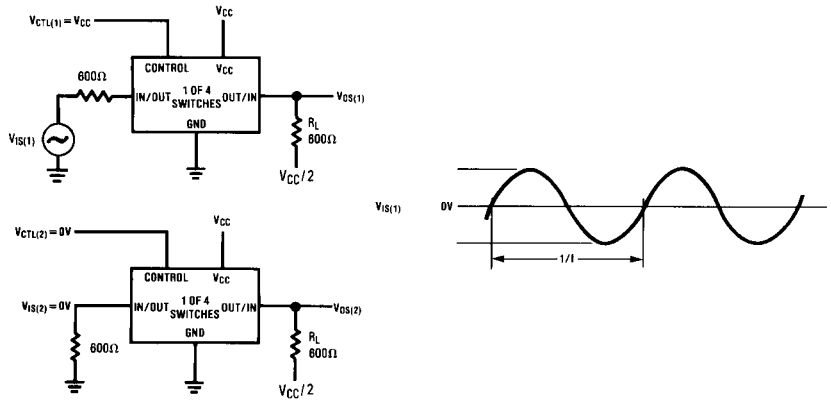


FIGURE 9. Crosstalk Between Any Two Switches

Crosstalk and Distortion Test Circuits (Continued)

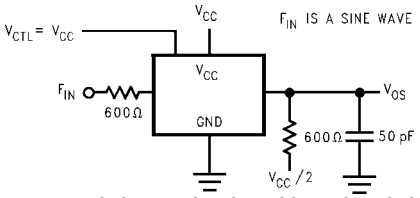


FIGURE 10. Switch OFF Signal Feedthrough Isolation

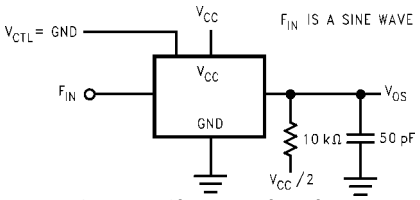
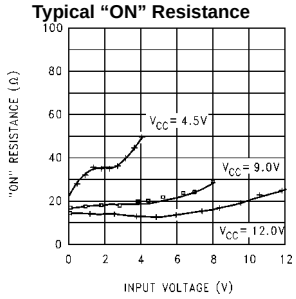


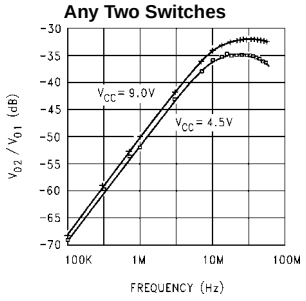
FIGURE 11. Sinewave Distortion

Typical Performance Characteristics

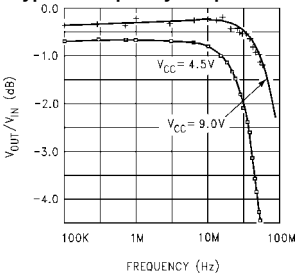
Typical "ON" Resistance



Typical Crosstalk Between Any Two Switches



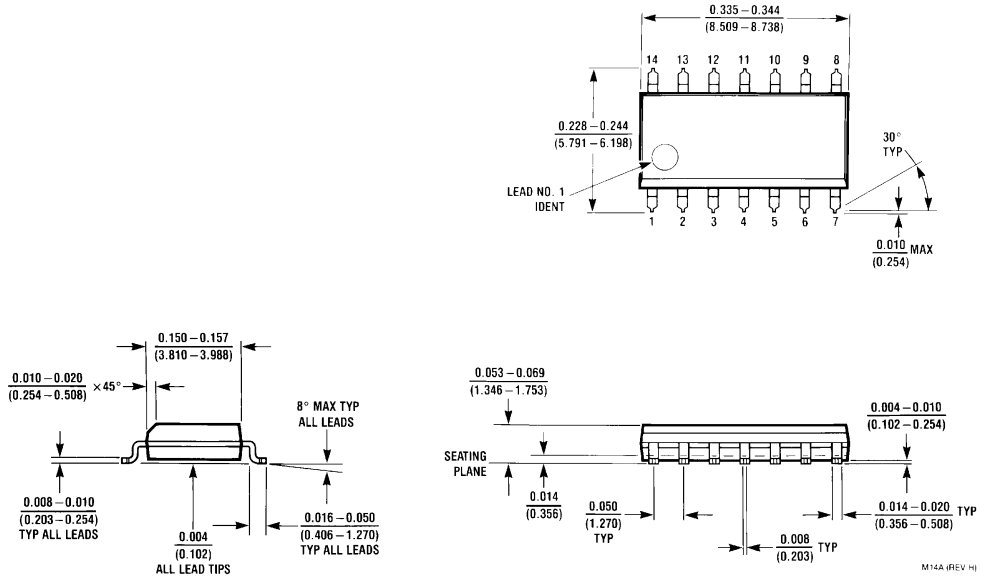
Typical Frequency Response



Special Considerations

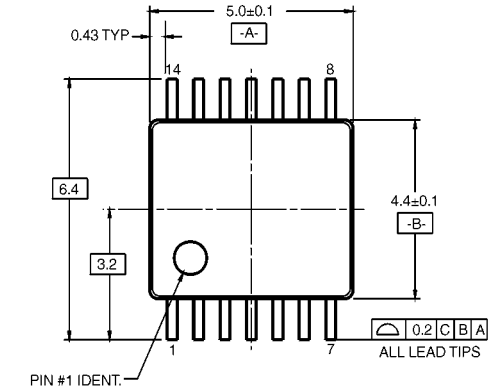
In certain applications the external load-resistor current may include both V_{CC} and signal line components. To avoid drawing V_{CC} current when switch current flows into the analog switch input pins, the voltage drop across the switch must not exceed 0.6V (calculated from the ON resistance).

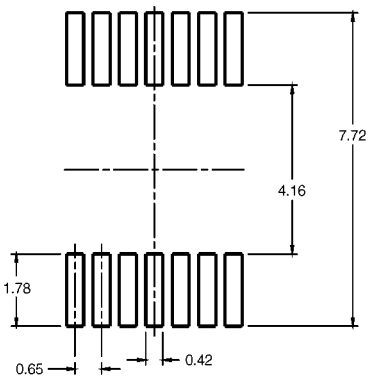
Physical Dimensions inches (millimeters) unless otherwise noted



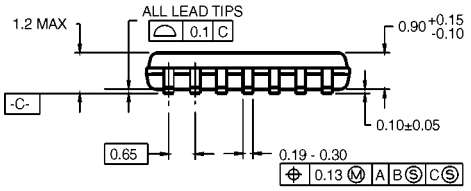
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

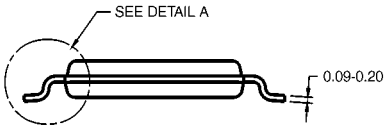
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

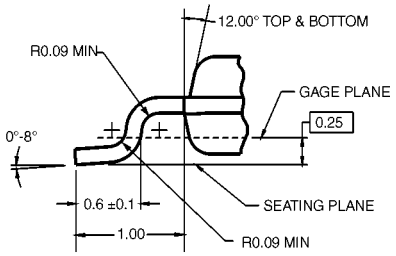




LAND PATTERN RECOMMENDATION







DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

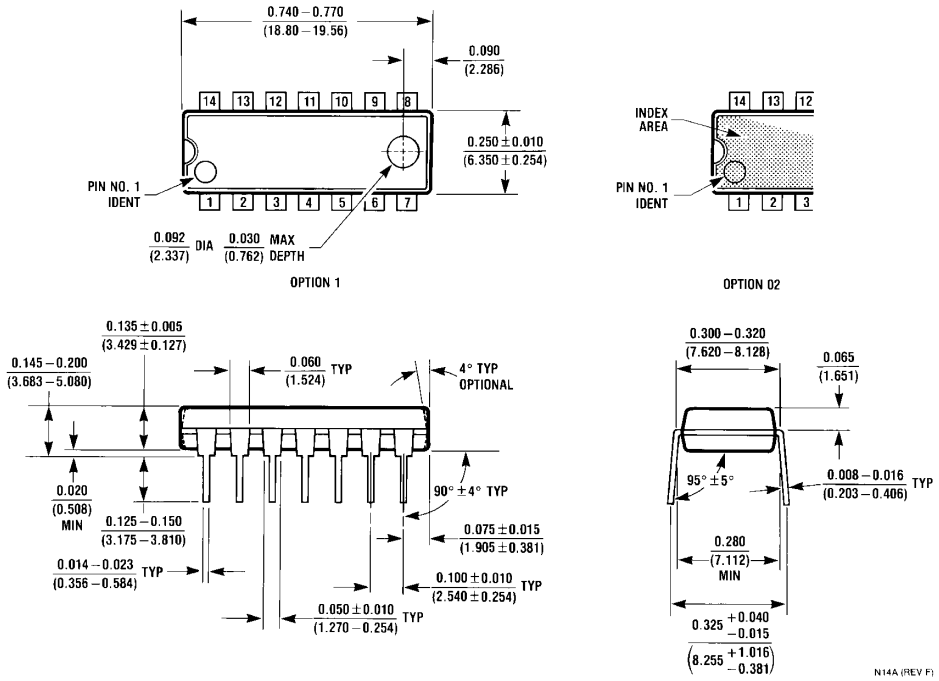
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

April 1994
Revised April 1999

74VHC4316
Quad Analog Switch with Level Translator

General Description

These devices are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Three supply pins are provided on the 4316 to implement a level translator which enables this circuit to operate with 0V–6V logic levels and up to ±6V analog switch levels. The 4316 also has a common enable input in addition to each switch's control which when HIGH will disable all switches to their off state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to V_{CC} and ground.

Features

- Typical switch enable time: 20 ns
- Wide analog input voltage range: ±6V
- Low "on" resistance: 50 typ. (V_{CC}–V_{EE} = 4.5V)
  30 typ. (V_{CC}–V_{EE} = 9V)
- Low quiescent current: 80 µA maximum (74VHC)
- Matched switch characteristics
- Individual switch controls plus a common enable
- Pin functional compatible with 74HC4316

Ordering Code:

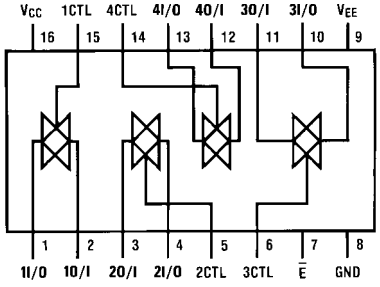
Order Number	Package Number	Package Description
74VHC4316M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC4316WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHC4316MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4316N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Truth Table

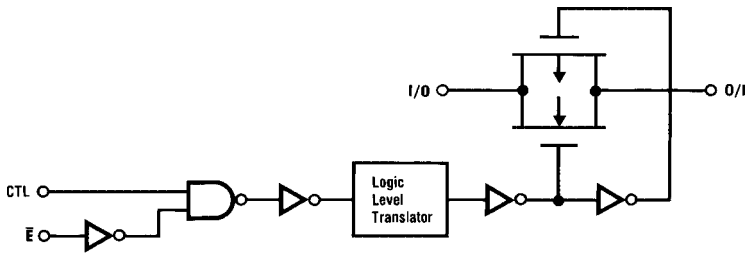
Inputs		Switch
$\overline{E}$	CTL	I/O–O/I
H	X	"OFF"
L	L	"OFF"
L	H	"ON"

Connection Diagram



Top View

Logic Diagram



Absolute Maximum Ratings (Note 1)

(Note 2)

Supply Voltage (V_{CC})	–0.5 to +7.5V
Supply Voltage (V_{EE})	+0.5 to –7.5V
DC Control Input Voltage (V_{IN})	–1.5 to V_{CC}+1.5V
DC Switch I/O Voltage (V_{IO})	V_{EE}–0.5 to V_{CC}+0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	–65°C to +150°C
Power Dissipation (P_D) (Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

		Min	Max	Units
Supply Voltage (V_{CC})		2	6	V
Supply Voltage (V_{EE})		0	–6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})		0	V_{CC}	V
Operating Temperature Range (T_A)		–40	+85	°C
Input Rise or Fall Times				
(t_r, t_f)	V_{CC} = 2.0V		1000	ns
	V_{CC} = 4.5V		500	ns
	V_{CC} = 6.0V		400	ns
	V_{CC} = 12.0V		250	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{EE}	V_{CC}	T_A = 25°C	T_A = –40°C to +85°C		Units
					Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage			2.0V		1.5	1.5	V
				4.5V		3.15	3.15	
				6.0V		4.2	4.2	
V_{IL}	Maximum LOW Level Input Voltage			2.0V		0.5	0.5	V
				4.5V		1.35	1.35	
				6.0V		1.8	1.8	
R_{ON}	Minimum "ON" Resistance (Note 5)	V_{CTL} = V_{IH}, I_S = 2.0 mA V_{IS} = V_{CC} to V_{EE} (*Figure 1*)	GND	4.5V	100	170	200	Ω
			–4.5V	4.5V	40	85	105	
			–6.0V	6.0V	30	70	85	
		V_{CTL} = V_{IH}, I_S = 2.0 mA V_{IS} = V_{CC} or V_{EE} (*Figure 1*)	GND	2.0V	100	180	215	
			GND	4.5V	40	80	100	
			–4.5V	4.5V	50	60	75	
			–6.0V	6.0V	20	40	60	
R_{ON}	Maximum "ON" Resistance Matching	V_{CTL} = V_{IH} V_{IS} = V_{CC} to V_{EE}	GND	4.5V	10	15	20	Ω
			–4.5V	4.5V	5	10	15	
			–6.0V	6.0V	5	10	15	
I_{IN}	Maximum Control Input Current	V_{IN} = V_{CC} or GND	GND	6.0V		±0.1	±1.0	µA
I_{IZ}	Maximum Switch "OFF" Leakage Current	V_{OS} = V_{CC} or V_{EE} V_{IS} = V_{EE} or V_{CC} V_{CTL} = V_{IL} (*Figure 2*)	GND	6.0V		±30	±300	nA
			–6.0V	6.0V		±50	±500	
I_{IZ}	Maximum Switch "ON" Leakage Current	V_{IS} = V_{CC} to V_{EE} V_{CTL} = V_{IH}, V_{OS} = OPEN (*Figure 3*)	GND	6.0V		±20	±75	nA
			–6.0V	6.0V		±30	±150	
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 µA	GND	6.0V		1.0	10	µA
			–6.0V	6.0V		4.0	40	

Note 4: For a power supply of 5V ±10% the worst case on resistances (R_{ON}) occurs for VHC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occurs for CMOS at the higher voltage and so the 5.5V values should be used.

Note 5: At supply voltages (V_{CC}–V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

AC Electrical Characteristics

V_{CC} = 2.0V – 6.0V, V_{EE} = 0V – 6V, C_L = 50 pF unless otherwise specified

Symbol	Parameter	Conditions	V_{EE}	V_{CC}	T_A=+25°C		T_A=–40°C to +85°C	Units
					Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation		GND	3.3V	15	30	37	
	Delay Switch In to		GND	4.5V	5	10	13	ns
	Out		–4.5V	4.5V	4	8	12	
			–6.0V	6.0V	3	7	11	
t_{PZL}, t_{PZH}	Maximum Switch Turn	R_L = 1 kΩ	GND	3.3V	25	97	120	
	"ON" Delay		GND	4.5V	20	35	43	ns
	(Control)		–4.5V	4.5V	15	32	39	
			–6.0V	6.0V	14	30	37	
t_{PHZ}, t_{PLZ}	Maximum Switch Turn	R_L = 1 kΩ	GND	3.3V	35	145	180	
	"OFF" Delay		GND	4.5V	25	50	63	ns
	(Control)		–4.5V	4.5V	20	44	55	
			–6.0V	6.0V	20	44	55	
t_{PZL}, t_{PZH}	Maximum Switch		GND	3.3V	27	120	150	
	Turn "ON" Delay		GND	4.5V	20	41	52	ns
	(Enable)		–4.5V	4.5V	19	38	48	
			–6.0V	6.0V	18	36	45	
t_{PLZ}, t_{PHZ}	Maximum Switch		GND	3.3V	42	155	190	
	Turn "OFF" Delay		GND	4.5V	28	53	67	ns
	(Enable)		–4.5V	4.5V	23	47	59	
			–6.0V	6.0V	21	47	59	
	Minimum Frequency	R_L = 600Ω, V_{IS} = 2V_{PP}	0V	4.5	40			
	Response (*Figure 7*)	at (V_{CC}–V_{EE}/2)	–4.5V	4.5V	100			MHz
	20 log (V_{OS}/V_{IS})= –3 dB	(Note 6)(Note 7)						
	Control to Switch	R_L = 600Ω, f = 1 MHz	0V	4.5V	100			
	Feedthrough Noise	C_L = 50 pF	–4.5V	4.5V	250			mV
	(*Figure 8*)	(Note 7)(Note 8)						
	Crosstalk Between	R_L = 600Ω, f = 1 MHz	0V	4.5V	–52			
	any Two Switches		–4.5V	4.5V	–50			dB
	(*Figure 9*)							
	Switch OFF Signal	R_L = 600Ω, f = 1 MHz						
	Feedthrough	V_{CTL} = V_{IL}	0V	4.5V	–42			dB
	Isolation		–4.5V	4.5V	–44			
	(*Figure 10*)	(Note 7)(Note 8)						
THD	Sinewave Harmonic	R_L = 10 KΩ, C_L = 50 pF,						
	Distortion	f = 1 KHz						%
	(*Figure 11*)	V_{IS} = 4 V_{PP}	0V	4.5V	0.013			
		V_{IS} = 8 V_{PP}	–4.5V	4.5V	0.008			
C_{IN}	Maximum Control				5			pF
	Input Capacitance							
C_{IN}	Maximum Switch				35			pF
	Input Capacitance							
C_{IN}	Maximum Feedthrough	V_{CTL} = GND			0.5			pF
	Capacitance							
C_{PD}	Power Dissipation				15			pF
	Capacitance							

Note 6: Adjust 0 dBm for f = 1 kHz (Null R_L/Ron Attenuation).

Note 7: V_{IS} is centered at V_{CC}–V_{EE}/2.

Note 8: Adjust for 0 dBm.

AC Test Circuits and Switching Time Waveforms

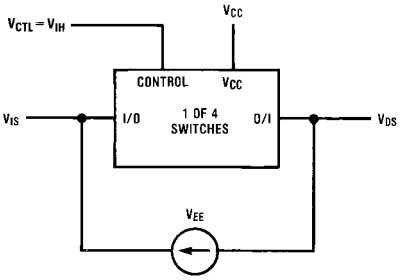


FIGURE 1. "ON" Resistance

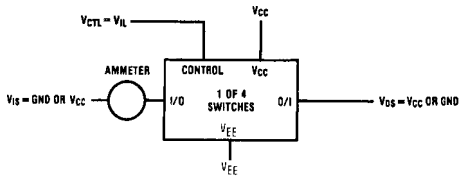


FIGURE 2. "OFF" Channel Leakage Current

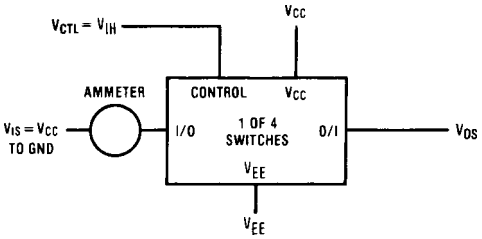


FIGURE 3. "ON" Channel Leakage Current

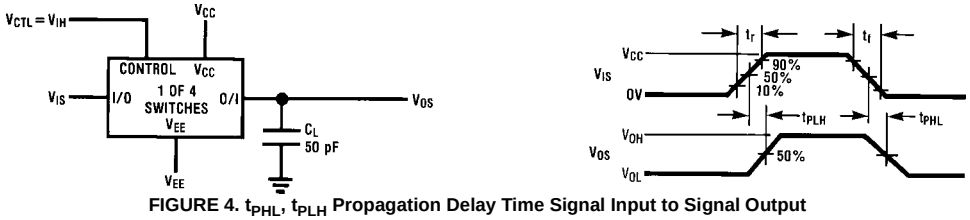


FIGURE 4. t_{PHL}, t_{PLH} Propagation Delay Time Signal Input to Signal Output

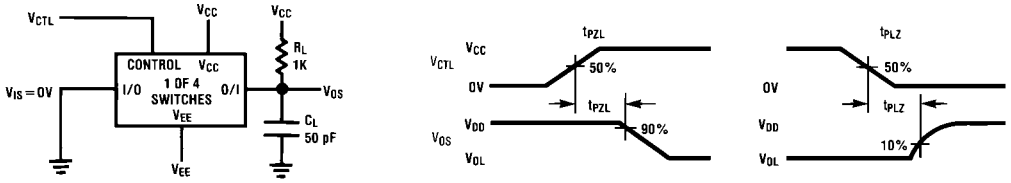


FIGURE 5. t_{PZL}, t_{PLZ} Propagation Delay Time Control to Signal Output

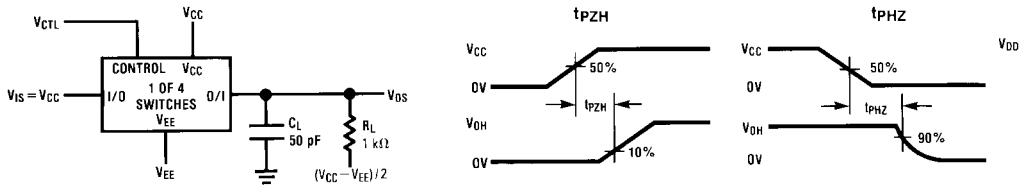


FIGURE 6. t_{PZH}, t_{PHZ} Propagation Delay Time Control to Signal Output

AC Test Circuits and Switching Time Waveforms (Continued)

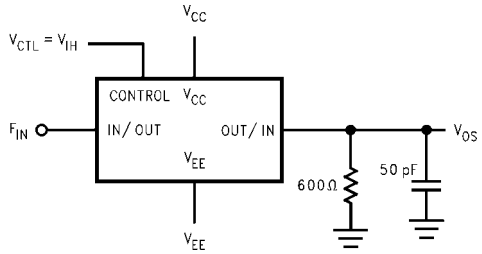


FIGURE 7. Frequency Response

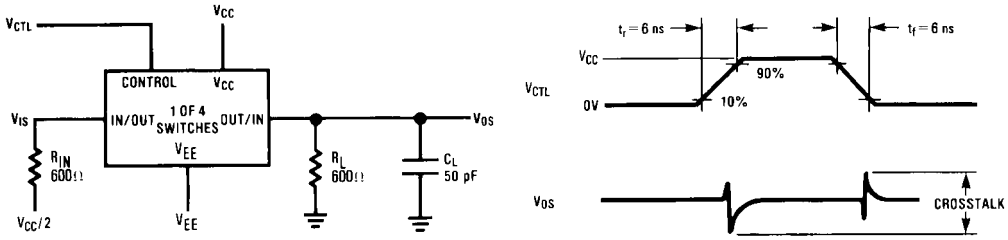


FIGURE 8. Crosstalk: Control Input to Signal Output

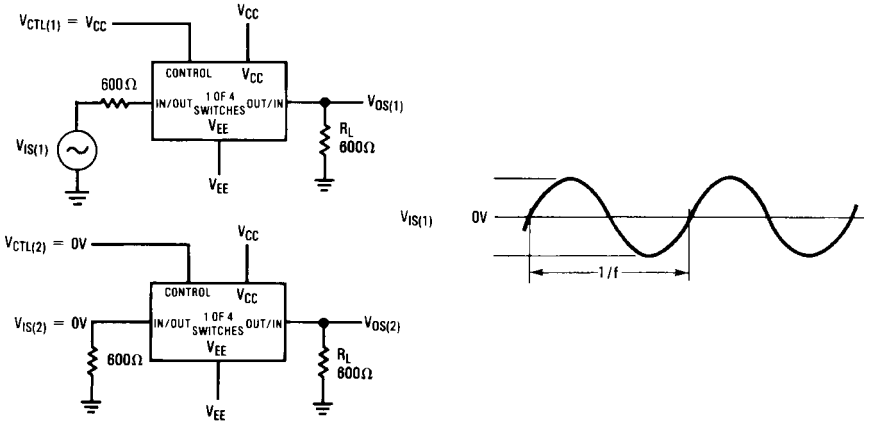


FIGURE 9. Crosstalk between Any Two Switches

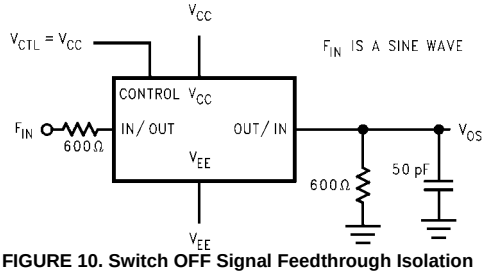


FIGURE 10. Switch OFF Signal Feedthrough Isolation

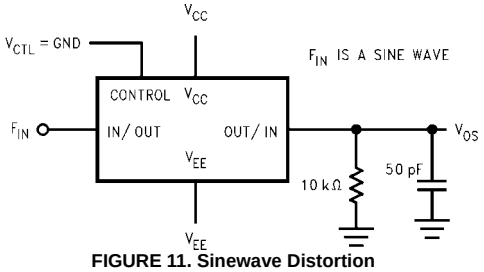
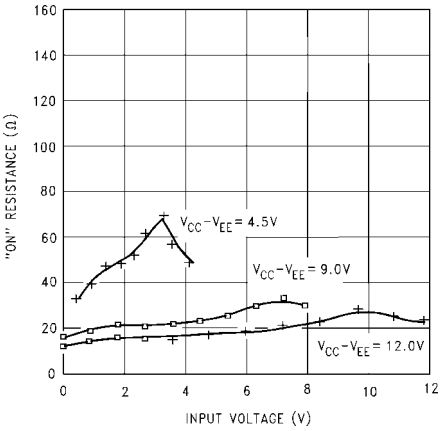


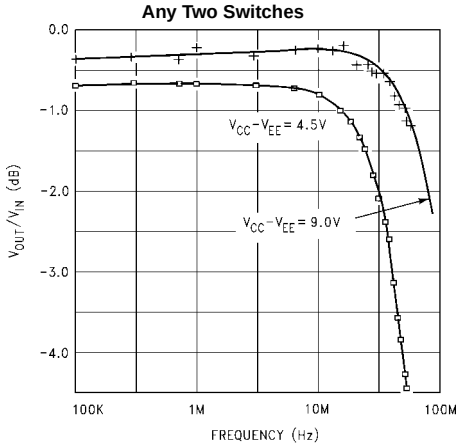
FIGURE 11. Sinewave Distortion

Typical Performance Characteristics

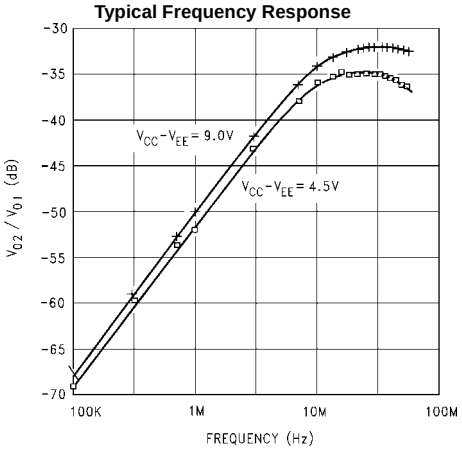
Typical "ON" Resistance



Typical Crosstalk between Any Two Switches



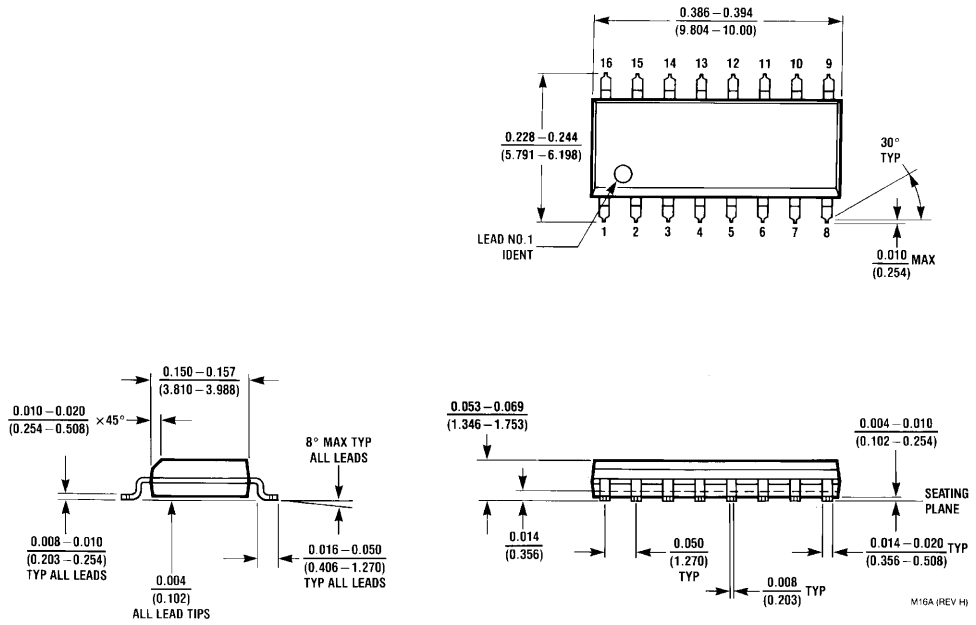
Typical Frequency Response



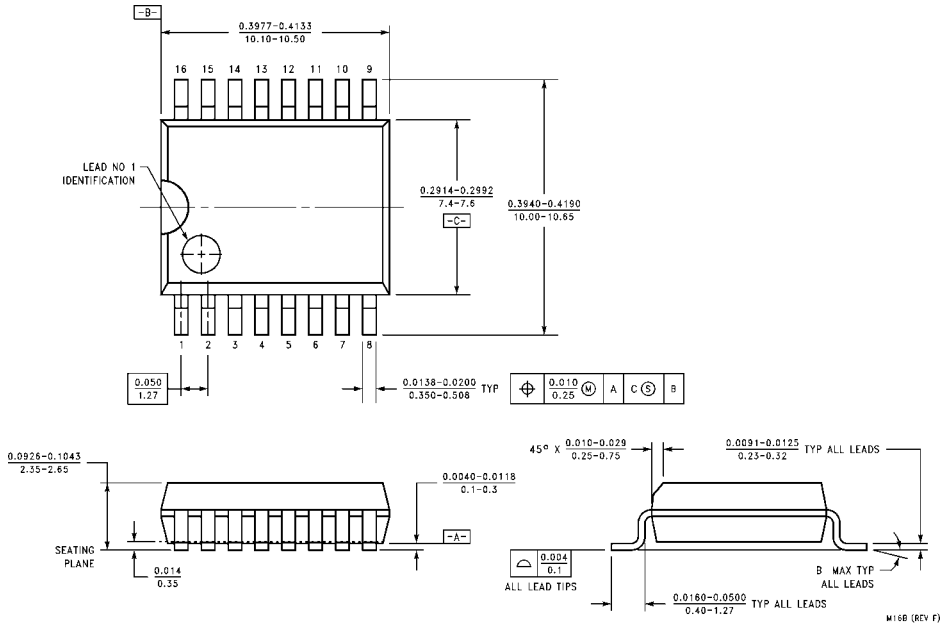
Special Considerations

In certain applications the external load-resistor current may include both V_{CC} and signal line components. To avoid drawing V_{CC} current when switch current flows into the analog switch input pins, the voltage drop across the switch must not exceed 0.6V (calculated from the ON resistance).

Physical Dimensions inches (millimeters) unless otherwise noted

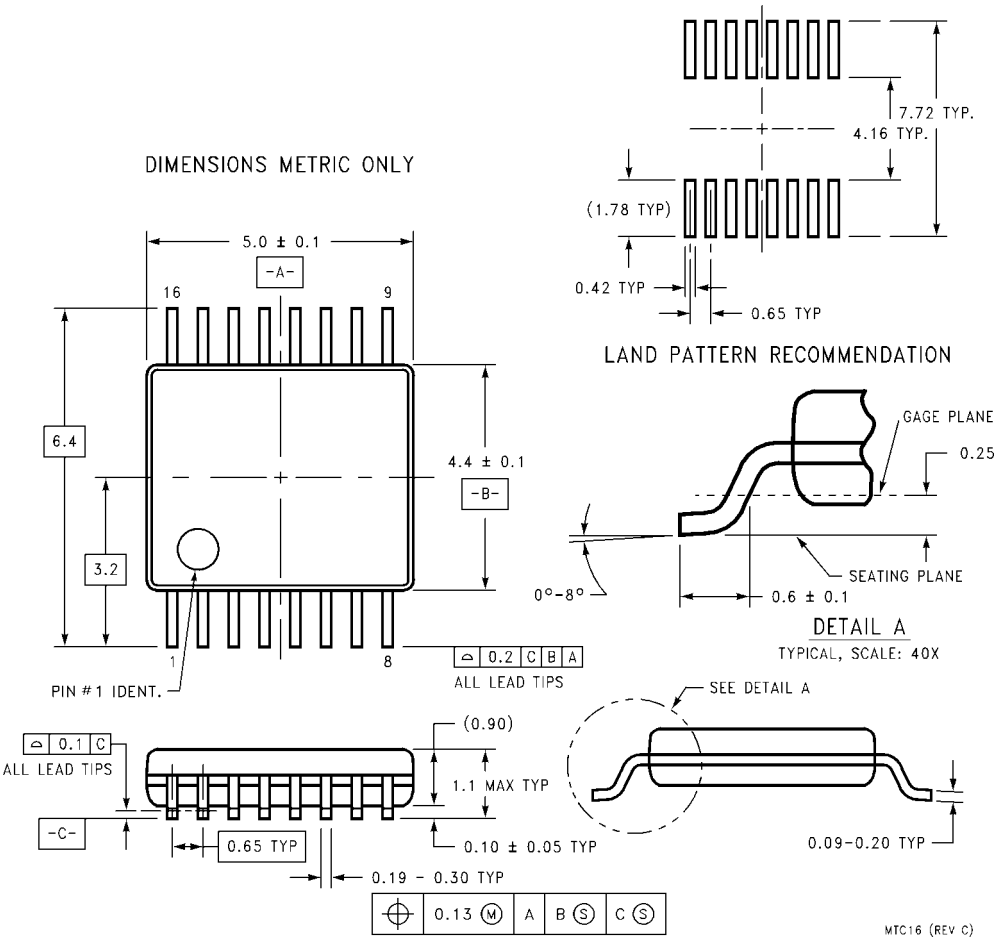


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



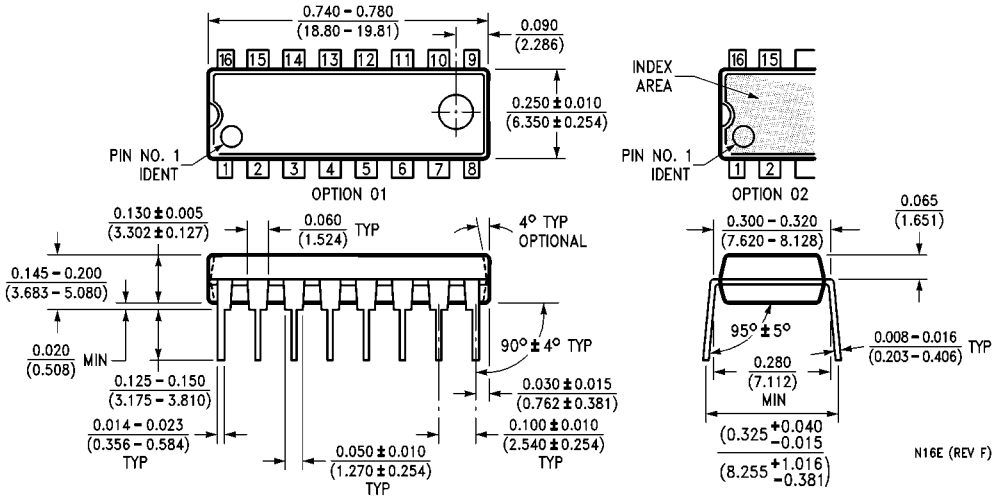
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M16B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

August 1993
Revised April 1999

74VHC541
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHC541 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC541 is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

This device is similar in function to the VHC244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

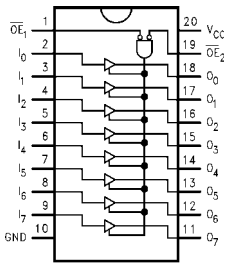
- High Speed: t_{PD} = 3.5 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.9V (typ)
- Pin and function compatible with 74HC541

Ordering Code:

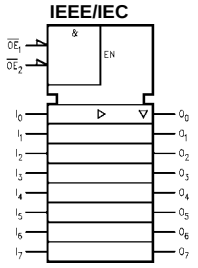
Order Number	Package Number	Package Description
74VHC541M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHC541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC541N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names	Descriptions
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0 - I_7	Inputs
O_0 - O_7	3-STATE Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.0	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum HIGH Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

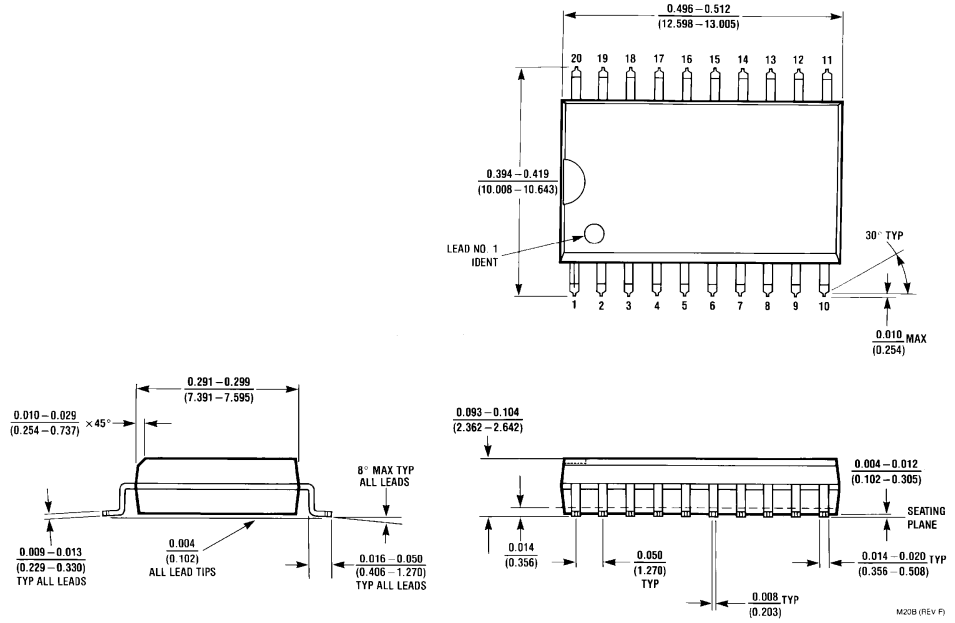
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		5.0	7.0	1.0	8.5	ns		C_L = 15 pF
t_{PHL}	Time			7.5	10.5	1.0	12.0			C_L = 50 pF
		5.0 ± 0.5		3.5	5.0	1.0	6.0	ns		C_L = 15 pF
				5.0	7.0	1.0	8.0			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		6.8	10.5	1.0	12.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			9.3	14.0	1.0	16.0			C_L = 50 pF
		5.0 ± 0.5		4.7	7.2	1.0	8.5	ns		C_L = 15 pF
				6.2	9.2	1.0	10.5			C_L = 50 pF
t_{PLZ}	3-STATE	3.3 ± 0.3		11.2	15.4	1.0	17.5	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Output	5.0 ± 0.5		6.0	8.8	1.0	10.0			C_L = 50 pF
	Disable Time									
t_{OSLH}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C_L = 50 pF
t_{OSHL}		5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 5)	

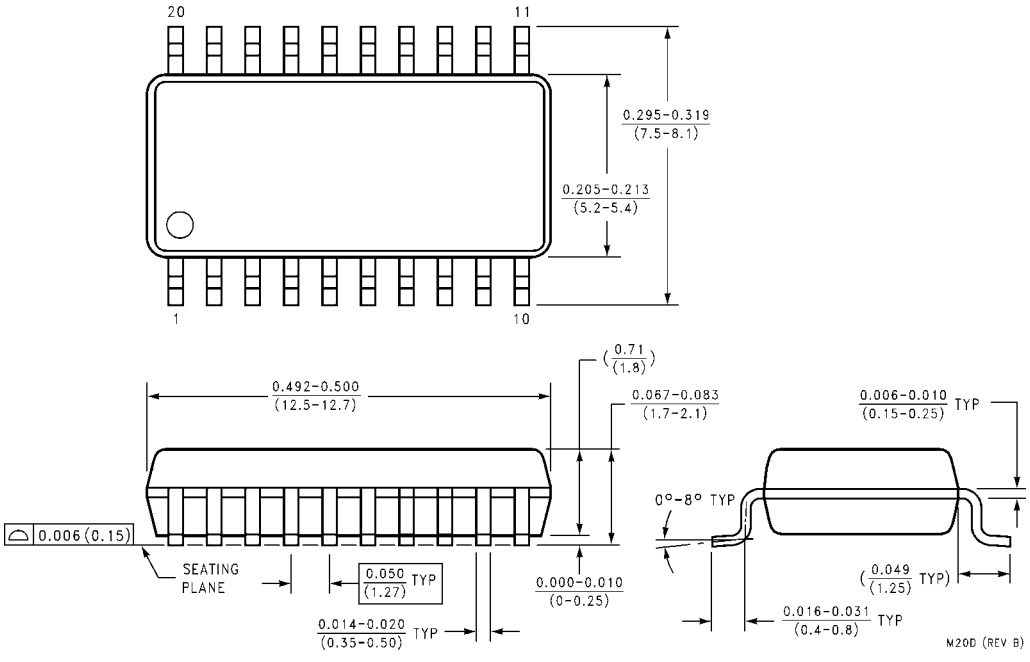
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

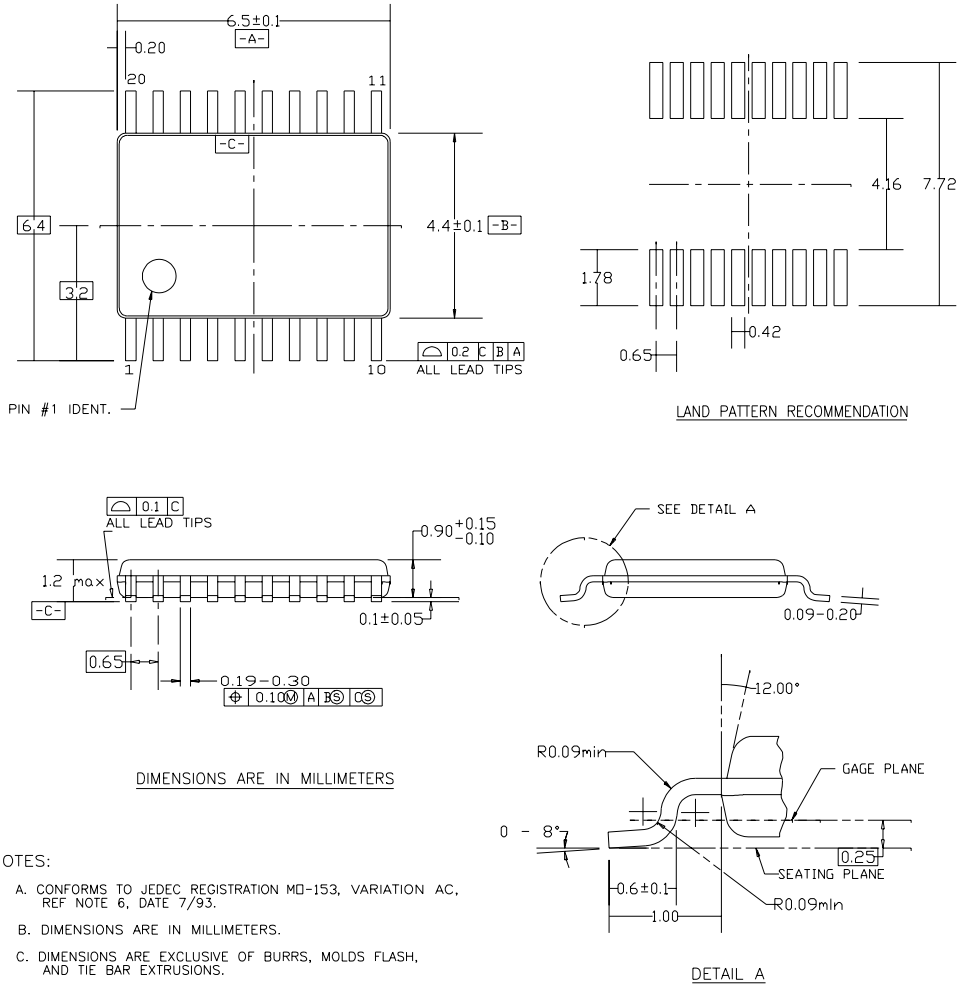


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

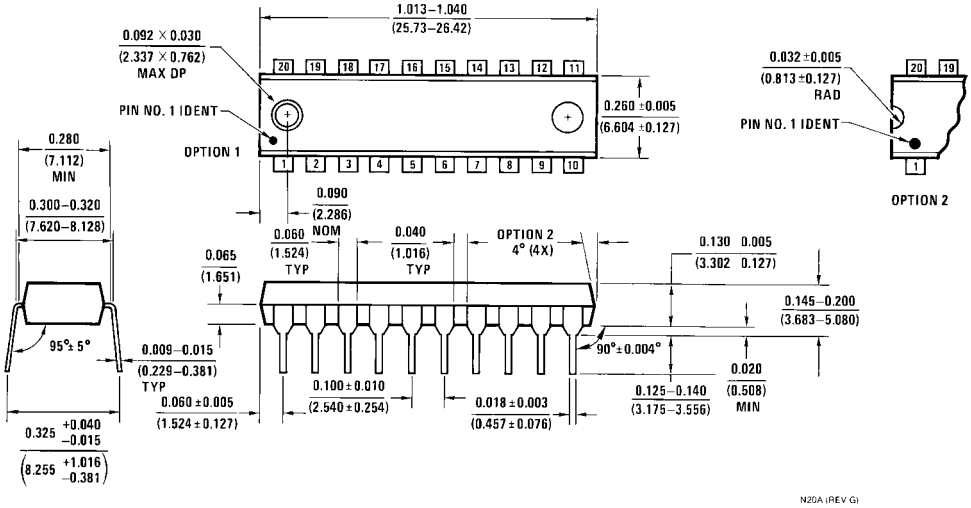
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1993
Revised April 1999

74VHC573
Octal D-Type Latch with 3-STATE Outputs

General Description

The VHC573 is an advanced high speed CMOS octal latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a latch enable input (LE) and an Output Enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

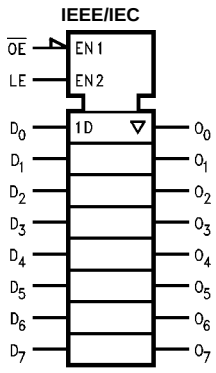
- High Speed: t_{PD} = 5.0 ns (typ) at V_{CC} = 5V
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power Down Protection is provided on all inputs
- Low Noise: V_{OLP} = 0.6V (typ)
- Low Power Dissipation: I_{CC} = 4 μA (Max) @ T_A = 25°C
- Pin and function compatible with 74HC573

Ordering Code:

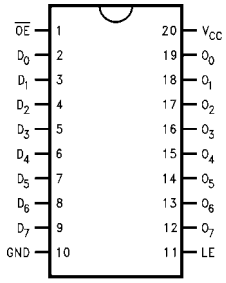
Order Number	Package Number	Package Description
74VHC573M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC573N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

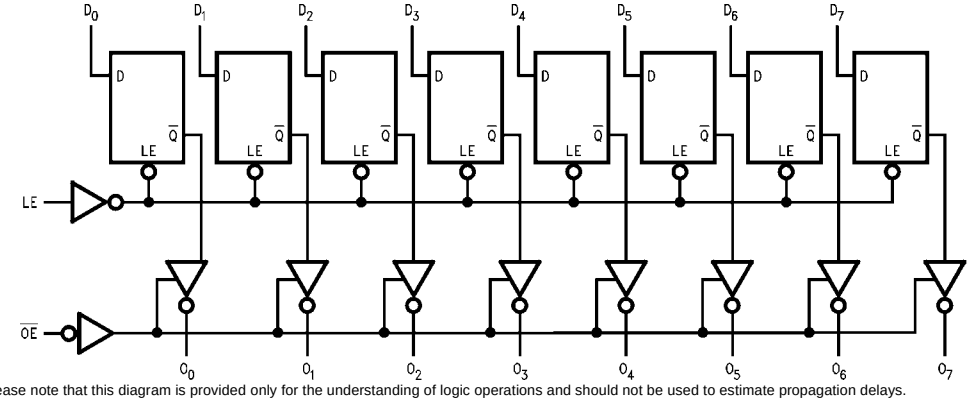
The VHC573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs, a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode, but, this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} +0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0 3.0 – 5.5	1.50 0.7 V_{CC}			1.50 0.7 V_{CC}		V		
V_{IL}	LOW Level Input Voltage	2.0 3.0 – 5.5			0.50 0.3 V_{CC}		0.50 0.3 V_{CC}	V		
V_{OH}	HIGH Level Output Voltage	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0 4.5	2.58 3.94			2.48 3.80		V		I_{OH} = −4 mA I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0 4.5			0.36 0.36		0.44 0.44	V		I_{OL} = 4 mA I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.0	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		7.6	11.9	1.0	14.0	ns		$C_L = 15$ pF
t_{PHL}	Time (LE to O_n)			10.1	15.4	1.0	17.5			$C_L = 50$ pF
		5.0 ± 0.5		5.0	7.7	1.0	9.0	ns		$C_L = 15$ pF
				6.5	9.7	1.0	11.0			$C_L = 50$ pF
t_{PLH}	Propagation Delay	3.3 ± 0.3		7.0	11.0	1.0	13.0	ns		$C_L = 15$ pF
t_{PHL}	Time ($D–O_n$)			9.5	14.5	1.0	16.5			$C_L = 50$ pF
		5.0 ± 0.5		4.5	6.8	1.0	8.0			$C_L = 15$ pF
				6.0	8.8	1.0	10.0			$C_L = 50$ pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		7.3	11.5	1.0	13.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			9.8	15.0	1.0	17.0			$C_L = 50$ pF
		5.0 ± 0.5		5.2	7.7	1.0	9.0	ns		$C_L = 15$ pF
				6.7	9.7	1.0	11.0			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		10.7	14.5	1.0	16.5	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time	5.0 ± 0.5		6.7	9.7	1.0	11.0			$C_L = 50$ pF
t_{OSLH}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	$C_L = 50$ pF
t_{OSHL}		5.0 ± 0.5			1.0		1.0			$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			29				pF	(Note 5)	

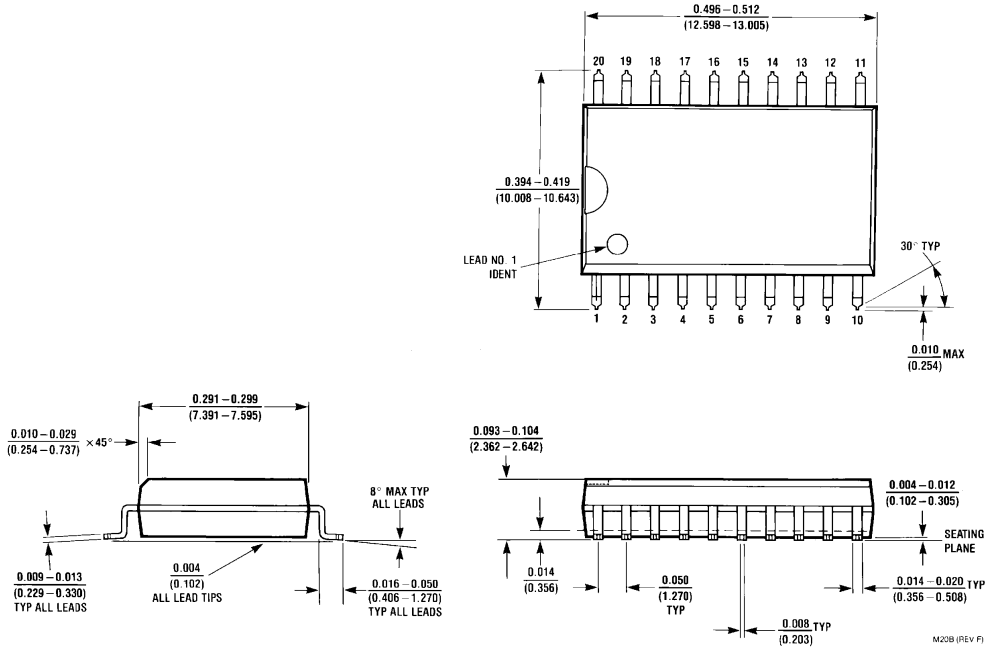
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per Latch). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 21 + 8n.

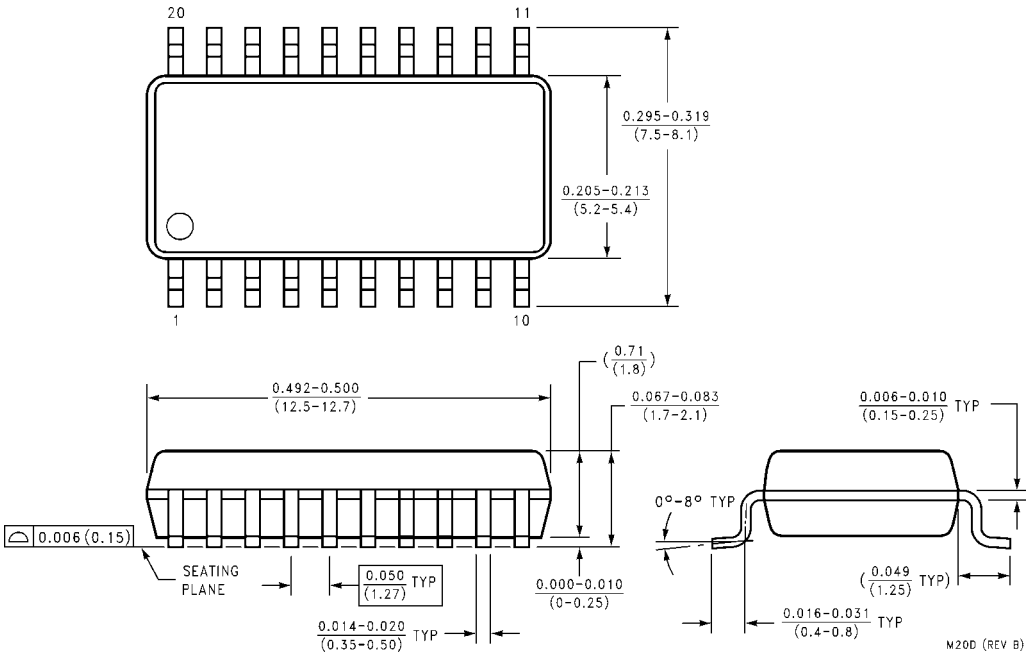
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
t_w(H)	Minimum Pulse	3.3 ± 0.3	5.0			5.0		ns
t_w(L)	Width (LE)	5.0 ± 0.5	5.0			5.0		
t_S	Minimum Setup Time	3.3 ± 0.3	3.5			3.5		ns
		5.0 ± 0.5	3.5			3.5		
t_H	Minimum Hold Time	3.3 ± 0.3	1.5			1.5		ns
		5.0 ± 0.5	1.5			1.5		

Physical Dimensions inches (millimeters) unless otherwise noted

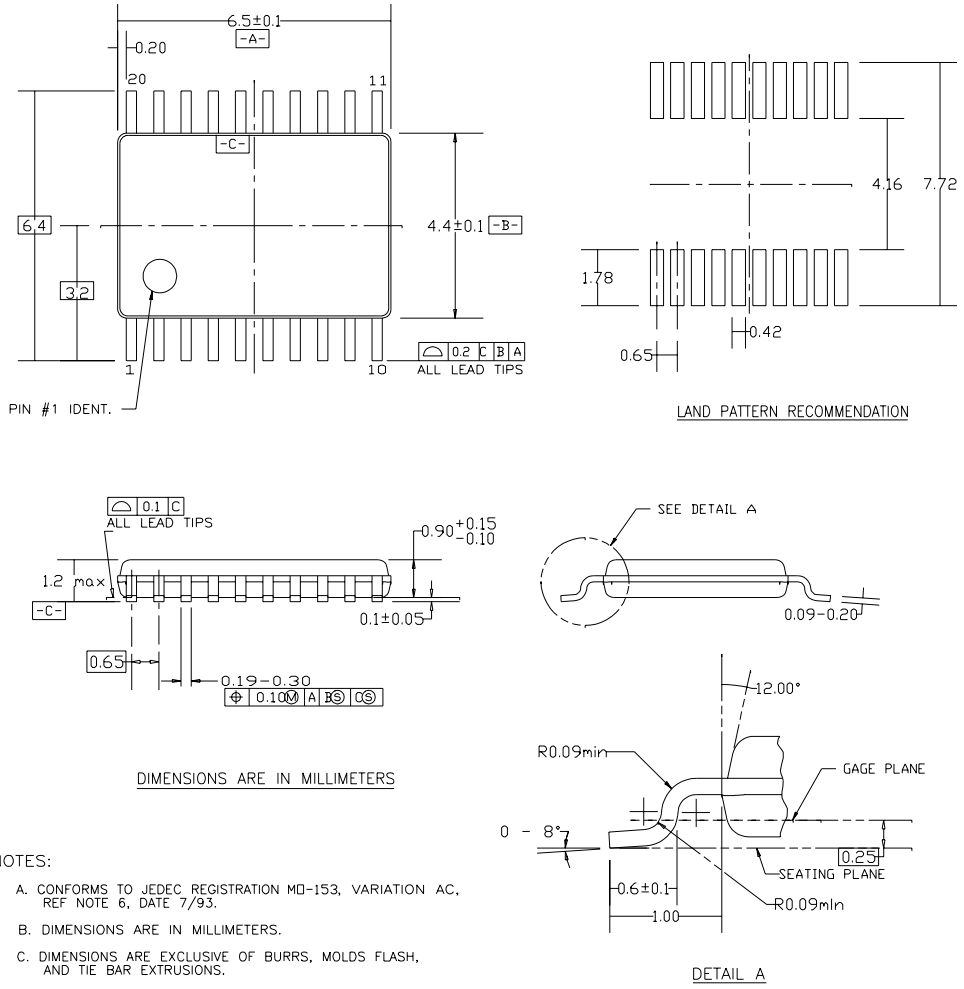


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

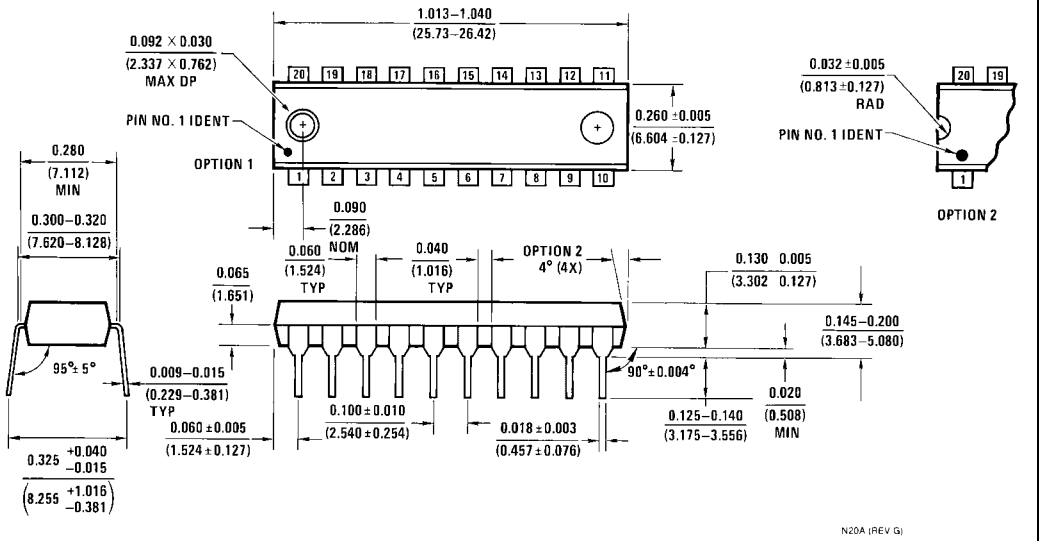
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1993
Revised April 1999

74VHC574
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The VHC574 is an advanced high speed CMOS octal flip-flop with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type flip-flop is controlled by a clock input (CP) and an output enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

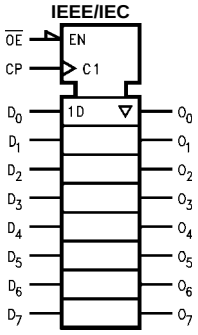
- High Speed: t_{PD} = 5.6 ns (typ) at V_{CC} = 5V
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power Down Protection is provided on all inputs
- Low Noise: V_{OLP} = 0.6V (typ)
- Low Power Dissipation: I_{CC} = 4 μA (Max) @ T_A = 25°C
- Pin and Function Compatible with 74HC574

Ordering Code:

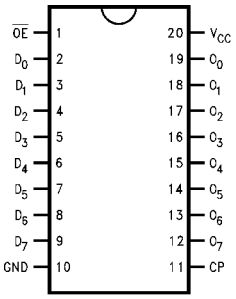
Order Number	Package Number	Package Description
74VHC574M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153
74VHC574N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

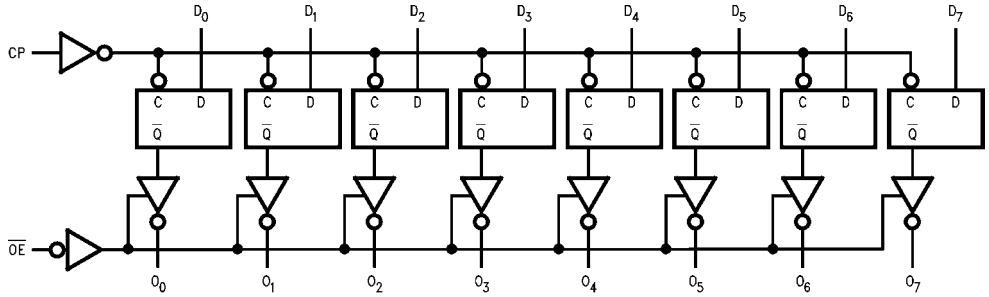
The VHC574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.0	1.2	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.0	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		8.5	13.2	1.0	15.5	ns		C_L = 15 pF
t_{PHL}	Time (CP to O_n)			11.0	16.7	1.0	19.0			C_L = 50 pF
		5.0 ± 0.5		5.6	8.6	1.0	10.0	ns		C_L = 15 pF
				7.1	10.6	1.0	12.0			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		8.2	12.8	1.0	15.0	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			10.7	16.3	1.0	18.5			C_L = 50 pF
		5.0 ± 0.5		5.9	9.0	1.0	10.5	ns		C_L = 15 pF
				7.4	11.0	1.0	12.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		11.0	15.0	1.0	17.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ± 0.5		7.1	10.1	1.0	11.5			C_L = 50 pF
t_{OSLH}	Output to	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C_L = 50 pF
t_{OSHL}	Output Skew	5.0 ± 0.5			1.0		1.0			C_L = 50 pF
f_{MAX}	Maximum Clock	3.3 ± 0.3	80	125		65		MHz		C_L = 15 pF
	Frequency		50	75		45				C_L = 50 pF
		5.0 ± 0.5	130	180		110				C_L = 15 pF
			85	115		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			28				pF	(Note 5)	

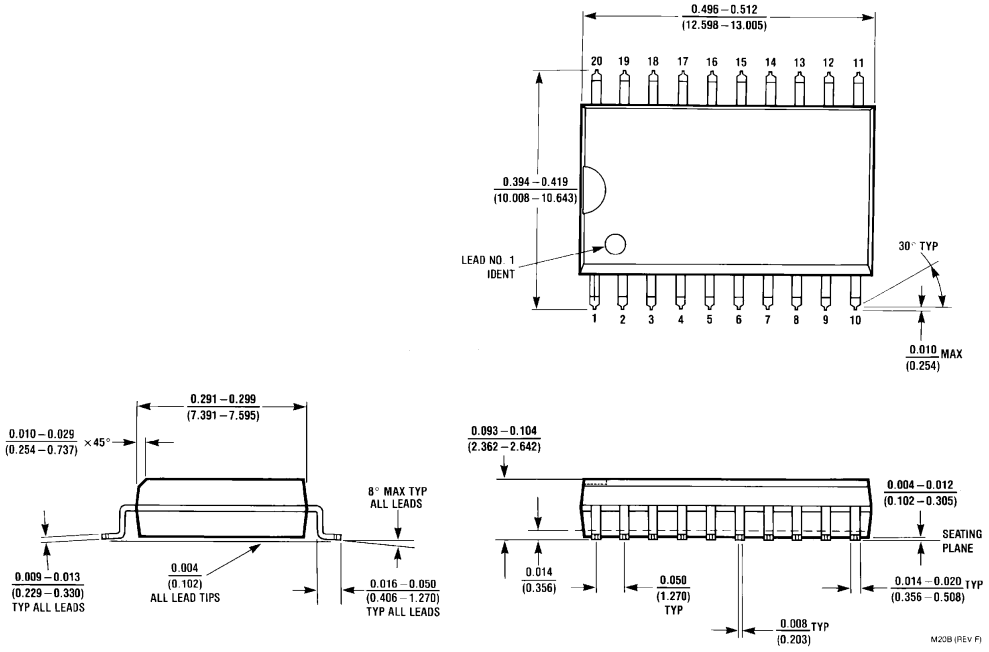
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 8n.

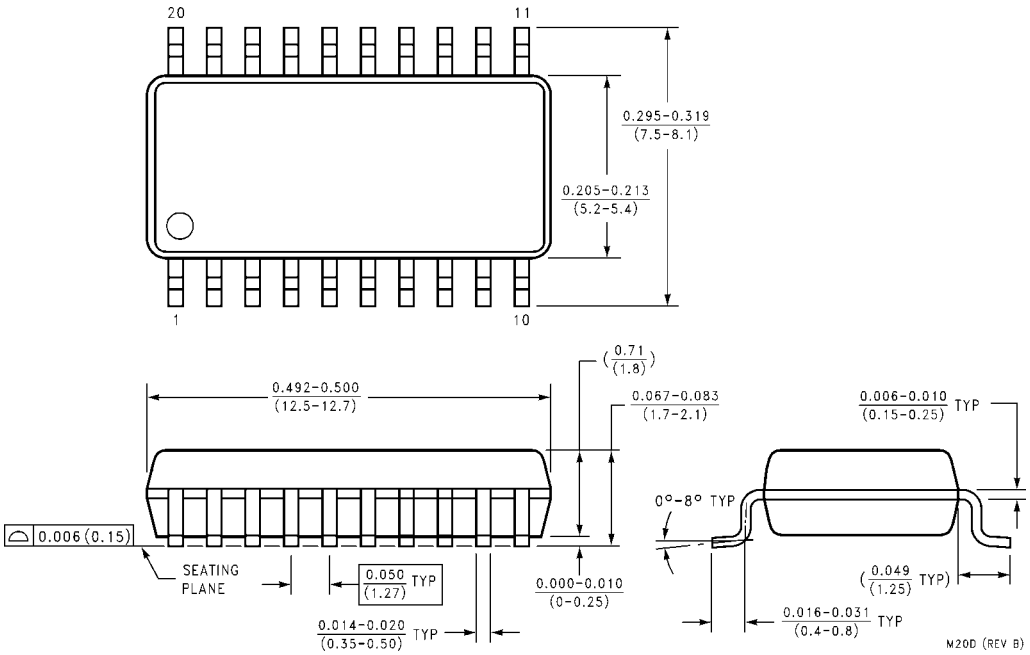
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
t_W(H)	Minimum Pulse Width (CP)	3.3 ± 0.3	5.0			5.0		ns
t_W(L)		5.0 ± 0.5	5.0			5.0		
t_S	Minimum Set-Up Time	3.3 ± 0.3	3.5			3.5		ns
		5.0 ± 0.5	3.5			3.5		
t_H	Minimum Hold Time	3.3 ± 0.3	1.5			1.5		
		5.0 ± 0.5	1.5			1.5		

Physical Dimensions inches (millimeters) unless otherwise noted

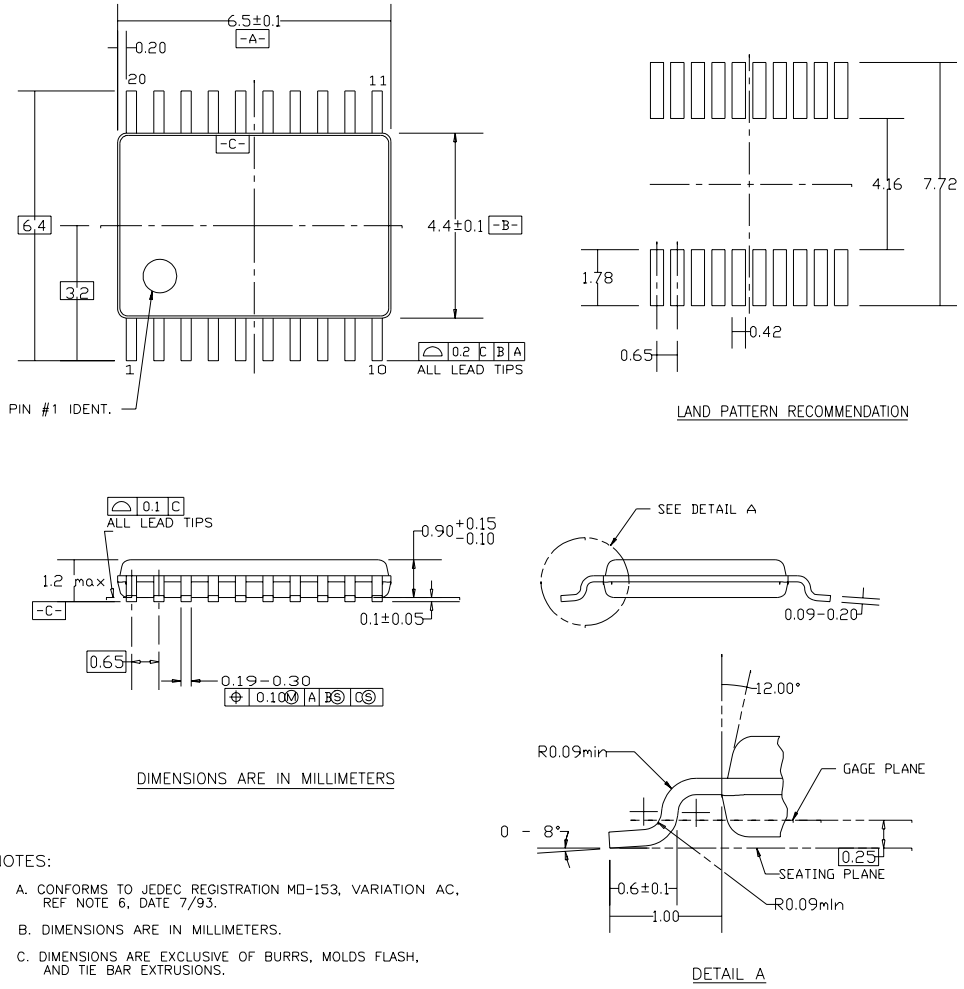


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

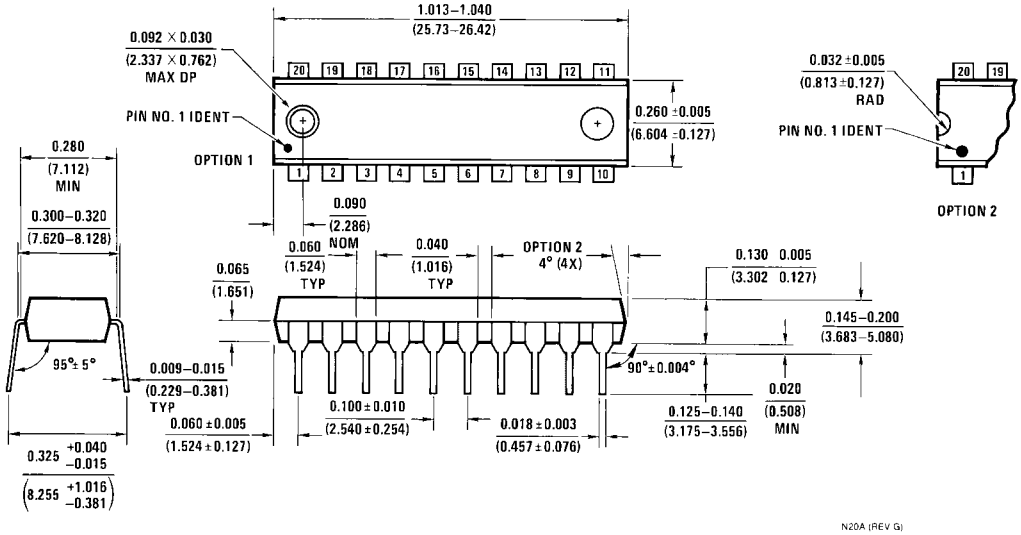
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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August 1993
Revised April 1999

74VHC595
8-Bit Shift Register with Output Latches

General Description

The VHC595 is an advanced high-speed CMOS Shift Register fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has eight 3-STATE outputs. Separate clocks are provided for both the shift register and the storage register. The shift register has a direct-overriding clear, serial input, and serial output (standard) pins for cascading. Both the shift register and storage register use positive-edge triggered clocks. If both clocks are connected together, the shift register state will always be one clock pulse ahead of the storage register.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

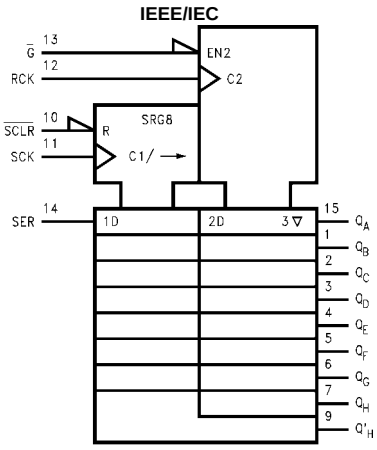
- High Speed: t_{PD} = 5.4 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.9V (typ)
- Pin and function compatible with 74HC595

Ordering Code:

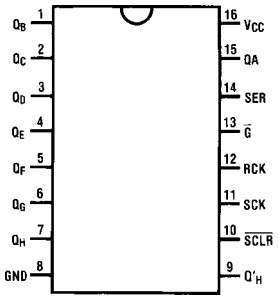
Order Number	Package Number	Package Description
74VHC595M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC595SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC595MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC595N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



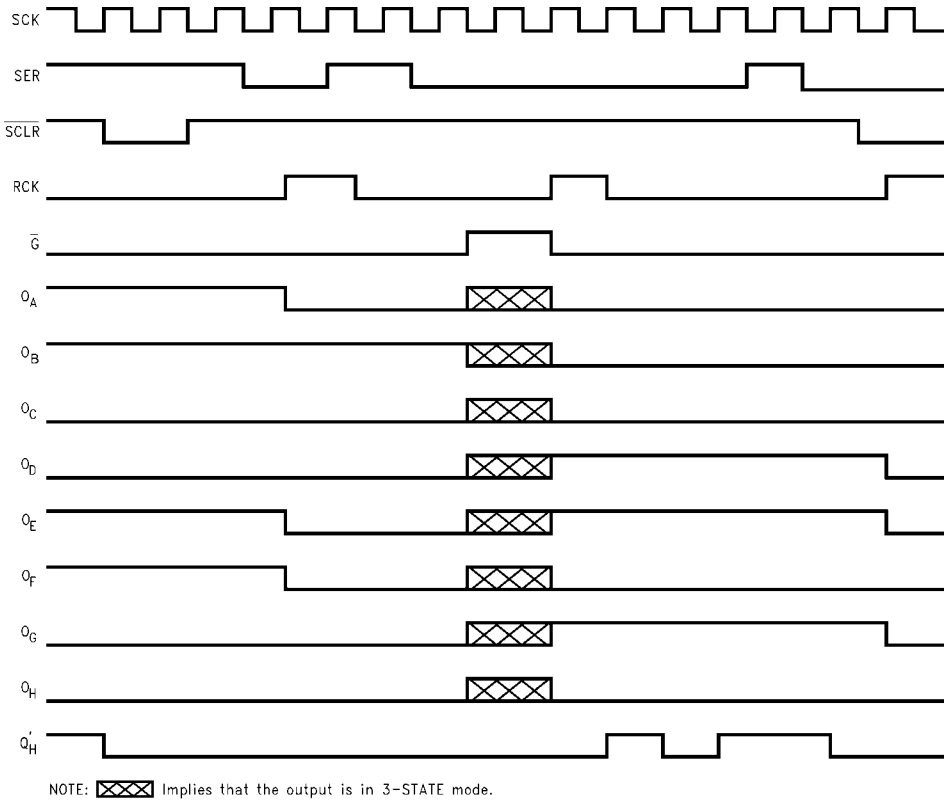
Pin Descriptions

Pin Names	Description
SER	Serial Data Input
SCK	Shift Register Clock Input (Active rising edge)
RCK	Storage Register Clock Input (Active rising edge)
$\overline{SCLR}$	Reset Input
$\overline{G}$	3-STATE Output Enable Input (Active LOW)
Q_A - Q_H	Parallel Data Outputs
Q'_H	Serial Data Output

Truth Table

Inputs					Function
SER	RCK	SCK	$\overline{SCLR}$	$\overline{G}$	
X	X	X	X	H	Q_A thru Q_H 3-STATE
X	X	X	X	L	Q_A thru Q_H outputs enabled
X	X	X	L	L	Shift Register cleared $Q'_H = 0$
L	X	↑	H	L	Shift Register clocked $Q_N = Q_{n-1}$, Q_0 = SER = L
H	X	↑	H	L	Shift Register clocked $Q_N = Q_{n-1}$, Q_0 = SER = H
X	↑	X	H	L	Contents of Shift Register transferred to output latches

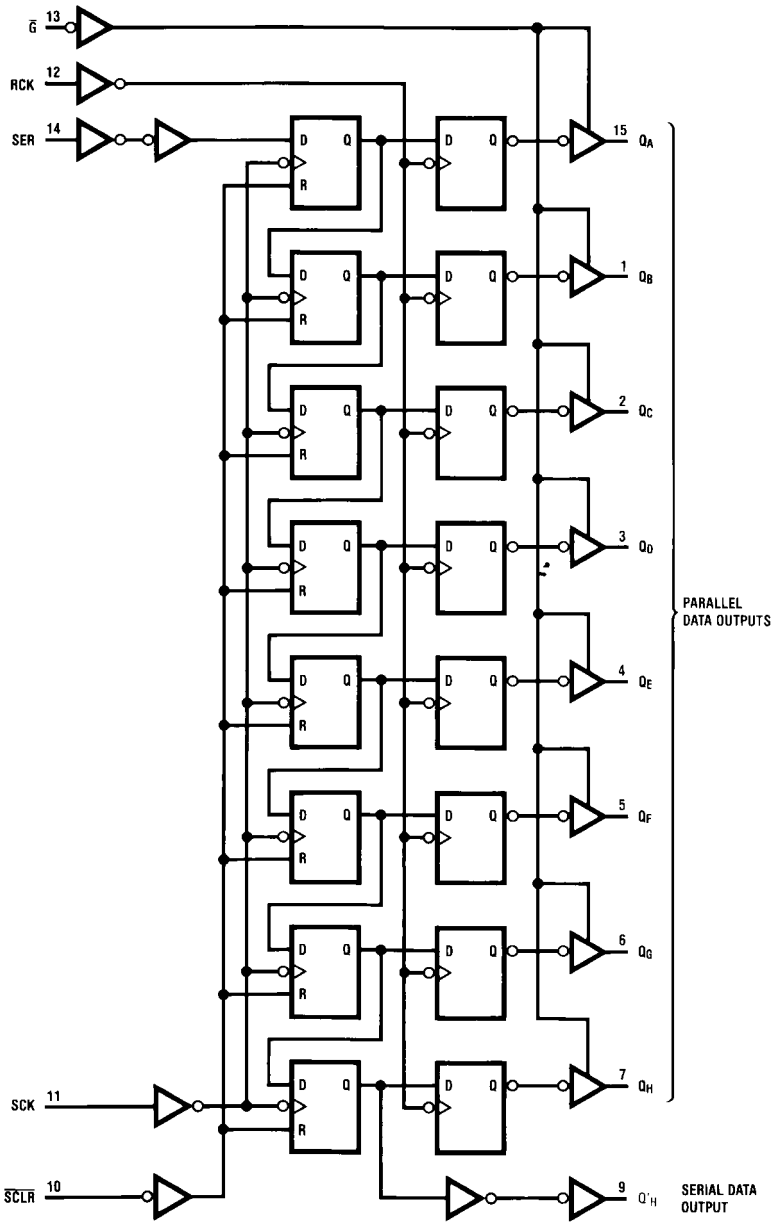
Timing Diagram



NOTE: ⊠ Implies that the output is in 3-STATE mode.

Logic Diagram

(positive logic)



Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{CC} or GND; V_{OUT} = V_{CC} or GND; $V_{IN}\overline{G}$ = V_{IH} or V_{IL}	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.9	−1.2	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH} t_{PHL}	Propagation Delay Time RCK to Q_A–Q_H	3.3 ± 0.3		7.7	11.9	1.0	13.5	ns		C_L = 15 pF
				10.2	15.4	1.0	17.0			C_L = 50 pF
		5.0 ± 0.5		5.4	7.4	1.0	8.5	ns		C_L = 15 pF
				6.9	9.4	1.0	10.5			C_L = 50 pF
t_{PLH} t_{PHL}	Propagation Delay Time SCK–Q'H	3.3 ± 0.3		8.8	13.0	1.0	15.0	ns		C_L = 15 pF
				11.3	16.5	1.0	18.5			C_L = 50 pF
		5.0 ± 0.5		6.2	8.2	1.0	9.4	ns		C_L = 15 pF
				7.7	10.2	1.0	11.4			C_L = 50 pF
t_{PHL}	Propagation Delay Time $\overline{SCLR}$ –Q'H	3.3 ± 0.3		8.4	12.8	1.0	13.7	ns		C_L = 15 pF
				10.9	16.3	1.0	17.2			C_L = 50 pF
		5.0 ± 0.5		5.9	8.0	1.0	9.1	ns		C_L = 15 pF
				7.4	10.0	1.0	11.1			C_L = 50 pF
t_{PZL} t_{PZH}	Output Enable Time $\overline{G}$ to Q_A–Q_H	3.3 ± 0.3		7.5	11.5	1.0	13.5	ns	R_L = 1 kΩ	C_L = 15 pF
				9.0	15.0	1.0	17.0			C_L = 50 pF
		5.0 ± 0.5		4.8	8.6	1.0	10.0	ns		C_L = 15 pF
				8.3	10.6	1.0	12.0			C_L = 50 pF
t_{PLZ} t_{PHZ}	Output Disable Time $\overline{G}$ to Q_A–Q_H	3.3 ± 0.3		12.1	15.7	1.0	16.2	ns	R_L = 1 kΩ	C_L = 50 pF
		5.0 ± 0.5		7.6	10.3	1.0	11.0			C_L = 50 pF
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	80	150		70		MHz		C_L = 15 pF
			55	130		50				C_L = 50 pF
		5.0 ± 0.5	135	185		115		MHz		C_L = 15 pF
			95	155		85				C_L = 50 pF
t_{OSLH} t_{OSHL}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C_L = 50 pF
		5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			5.0	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6.0				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			87				pF	(Note 5)	

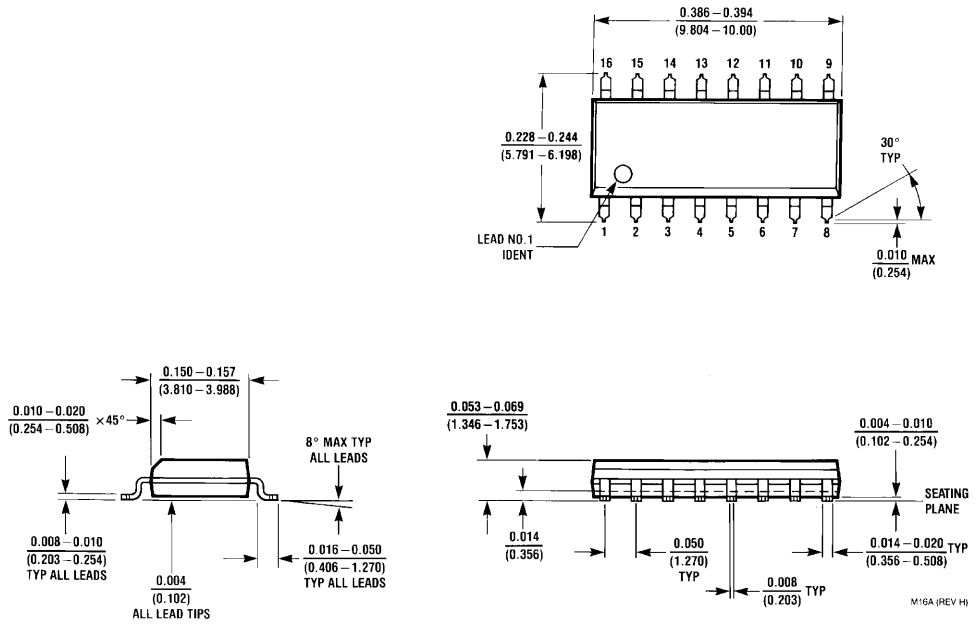
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH}$ max $- t_{PLH}$ min$|$; $t_{OSHL} = |t_{PHL}$ max $- t_{PHL}$ min$|$.

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}$.

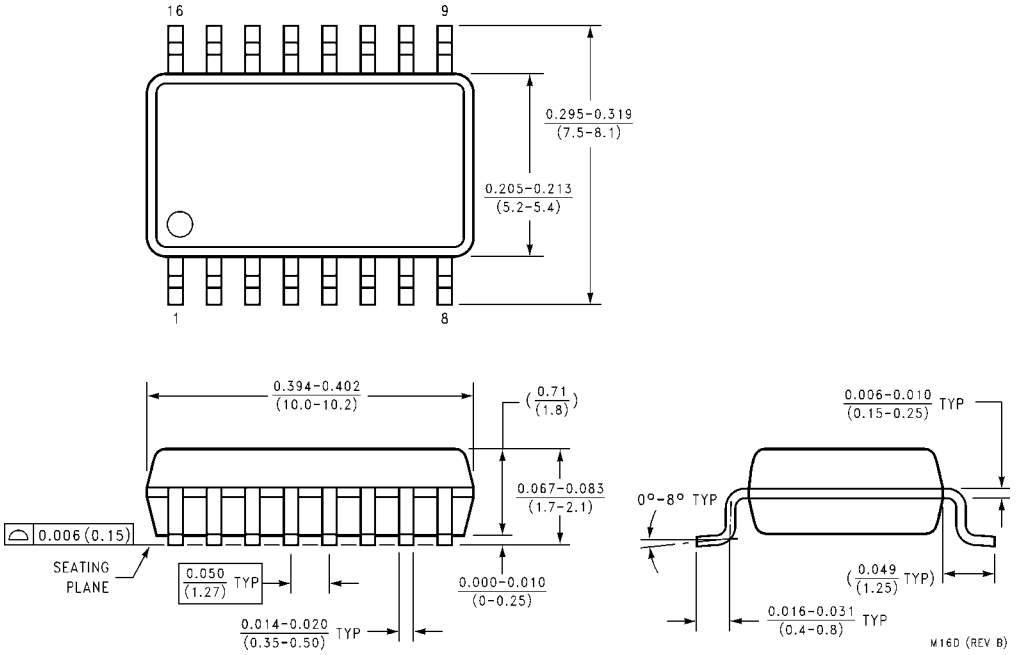
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$		Units
			Typ	Guaranteed Minimum		
t_S	Minimum Setup Time	3.3 ± 0.3		3.5	3.5	ns
	(SER–SCK)	5.0 ± 0.5		3.0	3.0	
t_S	Minimum Setup Time	3.3 ± 0.3		8.0	8.5	ns
	(SCK–RCK)	5.0 ± 0.5		5.0	5.0	
t_S	Minimum Setup Time	3.3 ± 0.3		8.0	9.0	ns
	($\overline{SCLR}$ –RCK)	5.0 ± 0.5		5.0	5.0	
t_H	Minimum Hold Time	3.3 ± 0.3		1.5	1.5	ns
	(SER–SCK)	5.0 ± 0.5		2.0	2.0	
t_H	Minimum Hold Time	3.3 ± 0.3		0.0	0.0	ns
	(SCK–RCK)	5.0 ± 0.5		0.0	0.0	
t_H	Minimum Hold Time	3.3 ± 0.3		0.0	0.0	ns
	($\overline{SCLR}$ –RCK)	5.0 ± 0.5		0.0	0.0	
$t_{W(L)}$	Minimum Pulse Width	3.3 ± 0.3		5.0	5.0	ns
	($\overline{SCLR}$)	5.0 ± 0.5		5.0	5.0	
$t_{W(L)}$	Minimum Pulse Width	3.3 ± 0.3		5.0	5.0	ns
$t_{W(H)}$	(SCK)	5.0 ± 0.5		5.0	5.0	
$t_{W(L)}$	Minimum Pulse Width	3.3 ± 0.3		5.0	5.0	ns
t_W(H)	(RCK)	5.0 ± 0.5		5.0	5.0	
t_{rem}	Minimum Removal Time	3.3 ± 0.3		3.0	3.0	ns
	($\overline{SCLR}$ –SCK)	5.0 ± 0.5		2.5	2.5	

Physical Dimensions inches (millimeters) unless otherwise noted

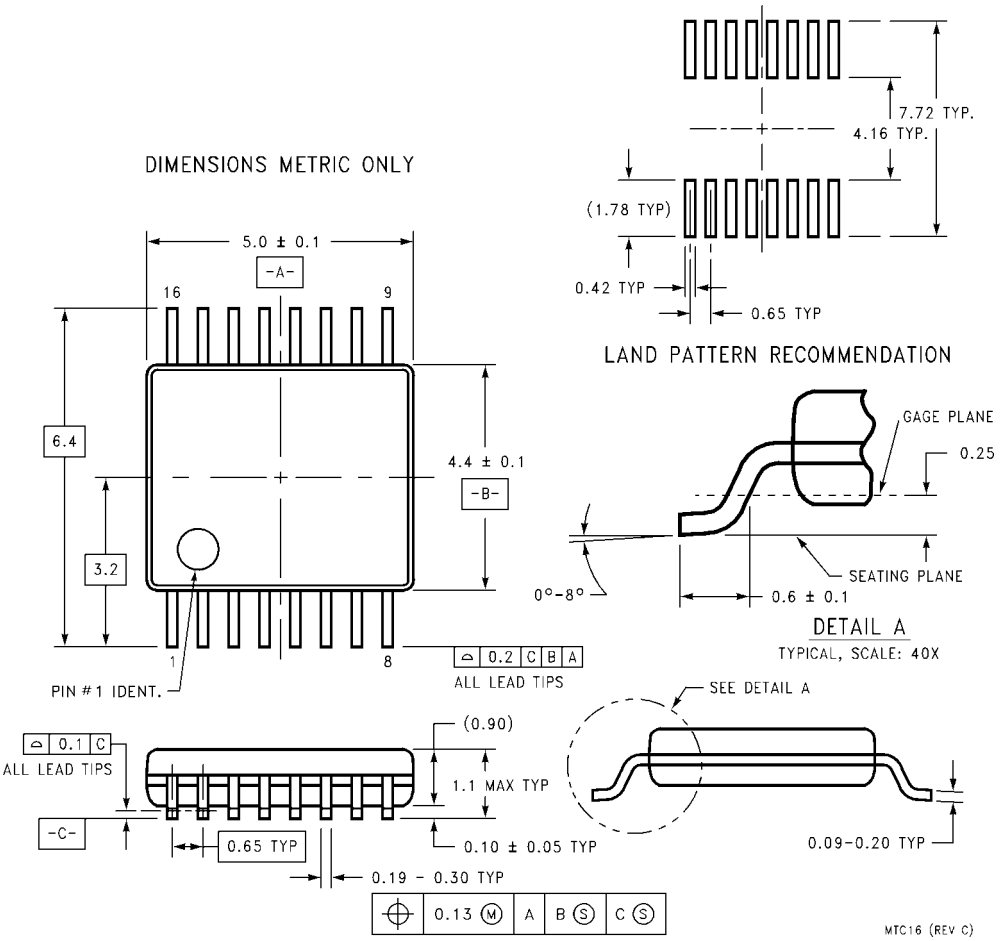


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



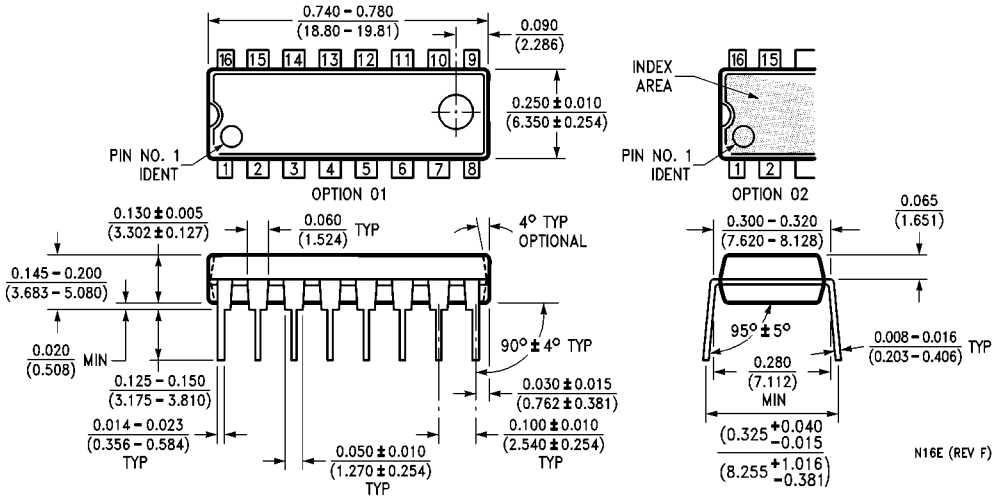
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

FAIRCHILD SEMICONDUCTOR™

October 1992
Revised March 1999

74VHC74
Dual D-Type Flip-Flop with Preset and Clear

General Description

The VHC74 is an advanced high speed CMOS Dual D-Type Flip-Flop fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The signal level applied to the D input is transferred to the Q output during the positive going transition of the CK pulse. $\overline{CLR}$ and $\overline{PR}$ are independent of the CK and are accomplished by setting the appropriate input LOW.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

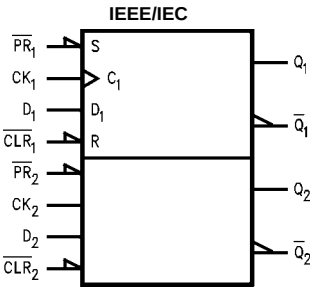
- High Speed: f_{MAX} = 170 MHz (typ) at T_A = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs
- Low power dissipation: I_{CC} = 2 μA (max) at T_A = 25°C
- Pin and function compatible with 74HC74

Ordering Code:

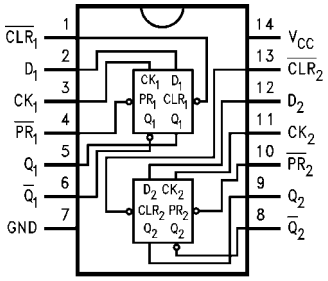
Order Number	Package Number	Package Description
74VHC74M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
74VHC74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC74MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC74N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CK_1, CK_2	Clock Pulse Inputs
$\overline{CLR}_1$, $\overline{CLR}_2$	Direct Clear Inputs
$\overline{PR}_1$, $\overline{PR}_2$	Direct Preset Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Output

Truth Table

Inputs				Outputs		Function
$\overline{CLR}$	$\overline{PR}$	D	CK	Q	$\overline{Q}$	
L	H	X	X	L	H	Clear
H	L	X	X	H	L	Preset
L	L	X	X	H (Note 1)	H (Note 1)	
H	H	L	↑	L	H	
H	H	H	↑	H	L	
H	H	X	↓	Q_n	$\overline{Q}_n$	No Change

Note 1: This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (HIGH) state.

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
Soldering (10 seconds)	260°C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	2.0V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading varaibles. Fairchild does not recommend operation outside databook specifications.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input	2.0	1.50			1.50		V		
	Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input	2.0			0.50		0.50	V		
	Voltage	3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
	Voltage	3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
	Voltage	3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock Frequency	3.3 ± 0.3	80	125		70		MHz	$C_L = 15$ pF
			50	75		45			$C_L = 50$ pF
		5.0 ± 0.5	130	170		110		MHz	$C_L = 15$ pF
			90	115		75			$C_L = 50$ pF
t_{PLH} t_{PHL}	Propagation Delay Time (CK-Q, $\overline{Q}$)	3.3 ± 0.3		6.7	11.9	1.0	14.0	ns	$C_L = 15$ pF
				9.2	15.4	1.0	17.5		$C_L = 50$ pF
		5.0 ± 0.5		4.6	7.3	1.0	8.5	ns	$C_L = 15$ pF
				6.1	9.3	1.0	10.5		$C_L = 50$ pF
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{CLR}$, $\overline{PR}$ -Q, $\overline{Q}$)	3.3 ± 0.3		7.6	12.3	1.0	14.5	ns	$C_L = 15$ pF
				10.1	15.8	1.0	18.0		$C_L = 50$ pF
		5.0 ± 0.5		4.8	7.7	1.0	9.0	ns	$C_L = 15$ pF
				6.3	9.7	1.0	11.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			25				pF	(Note 4)

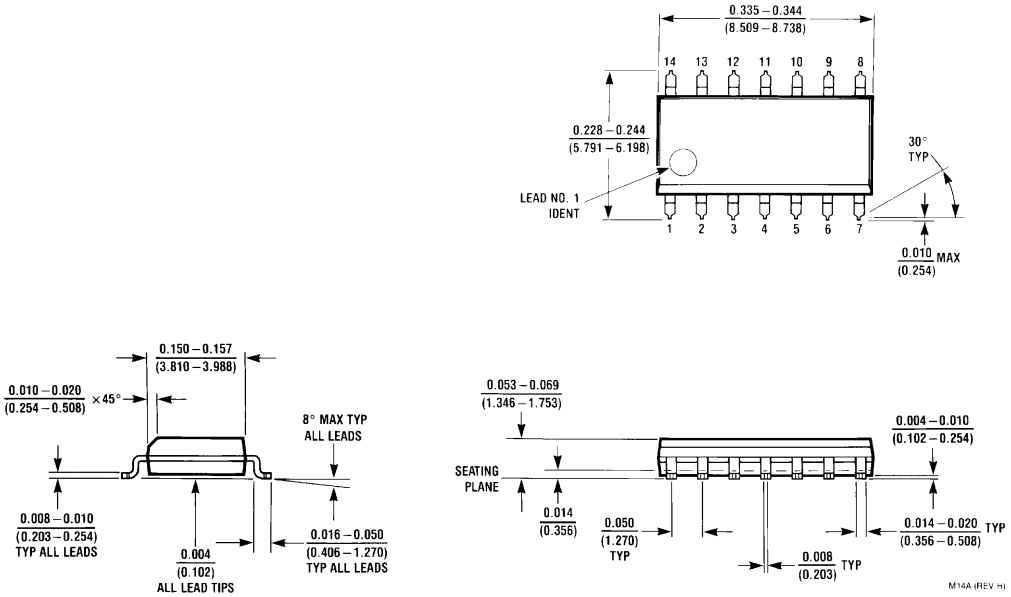
Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/2$ (per F/F).

AC Operating Requirements

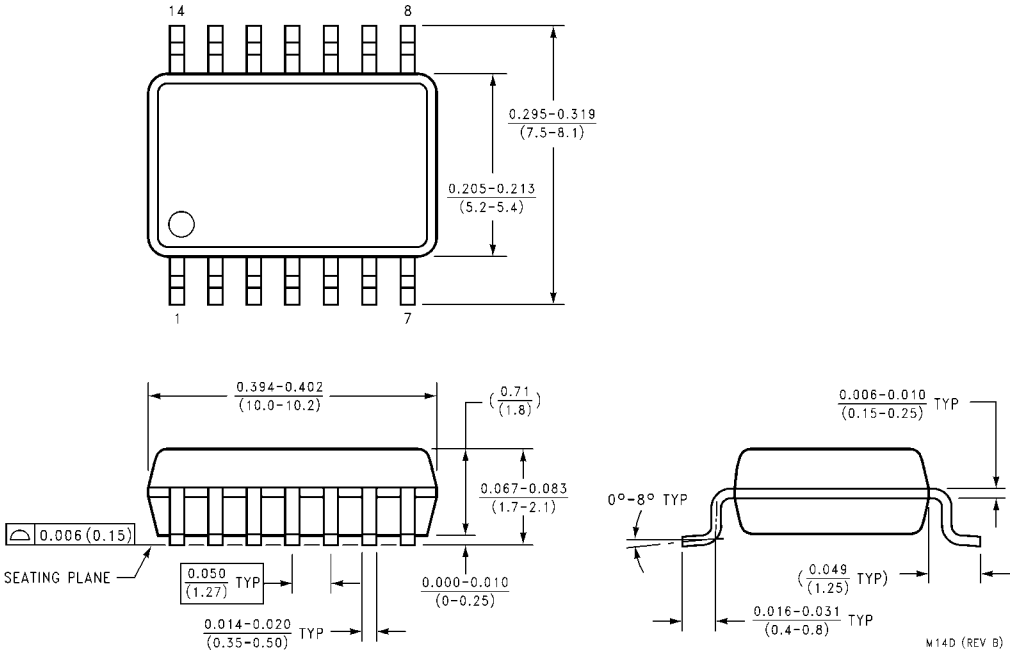
Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = 25°C$		$T_A = -40°C$ to $+85°C$	Units
			Typ	Guaranteed Minimum		
$t_W(L)$	Minimum Pulse Width (CK)	3.3		6.0	7.0	ns
$t_W(H)$		5.0		5.0	5.0	
$t_W(L)$	Minimum Pulse Width ($\overline{CLR}$, $\overline{PR}$)	3.3		6.0	7.0	ns
		5.0		5.0	5.0	
t_S	Minimum Setup Time	3.3		6.0	7.0	ns
		5.0		5.0	5.0	
t_H	Minimum Hold Time	3.3		0.5	0.5	ns
		5.0		0.5	0.5	
t_{REC}	Minimum Recovery Time ($\overline{CLR}$, $\overline{PR}$)	3.3		5.0	5.0	ns
		5.0		3.0	3.0	

Note 5: V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V

Physical Dimensions inches (millimeters) unless otherwise noted

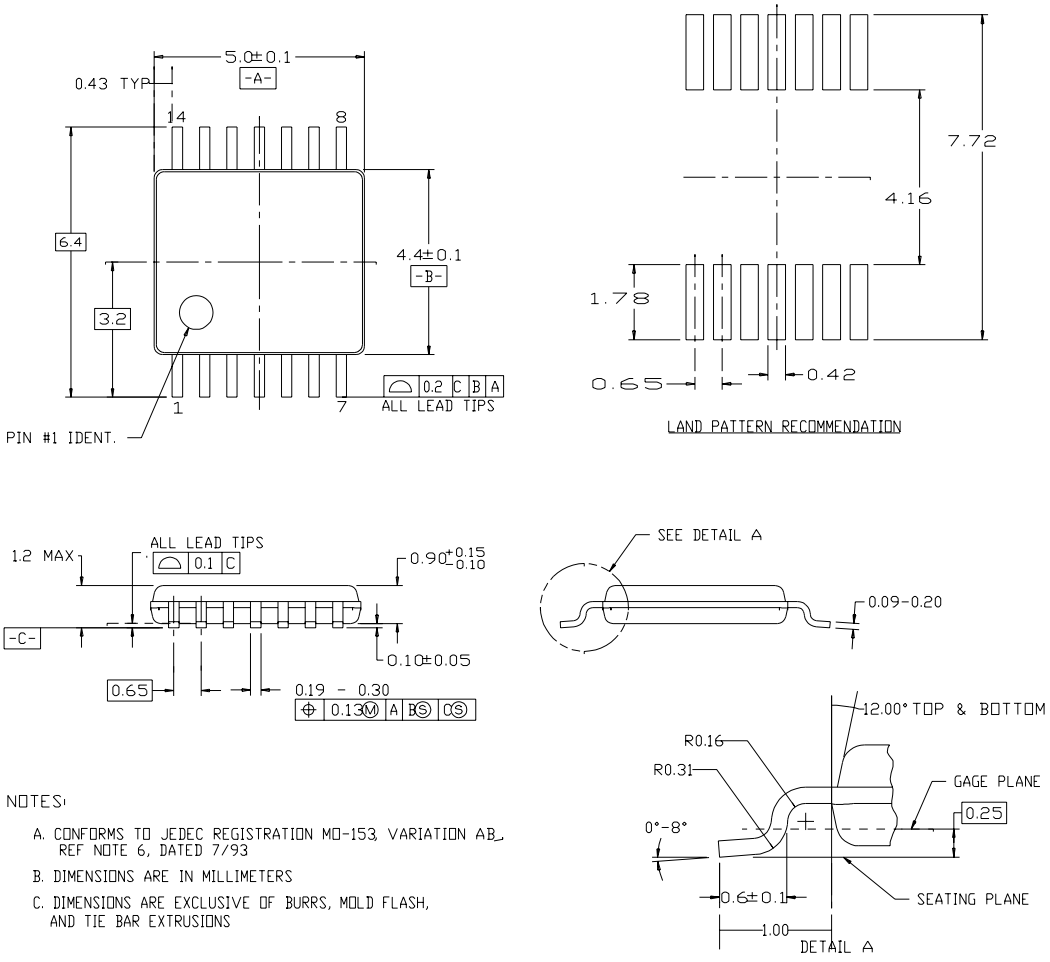


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

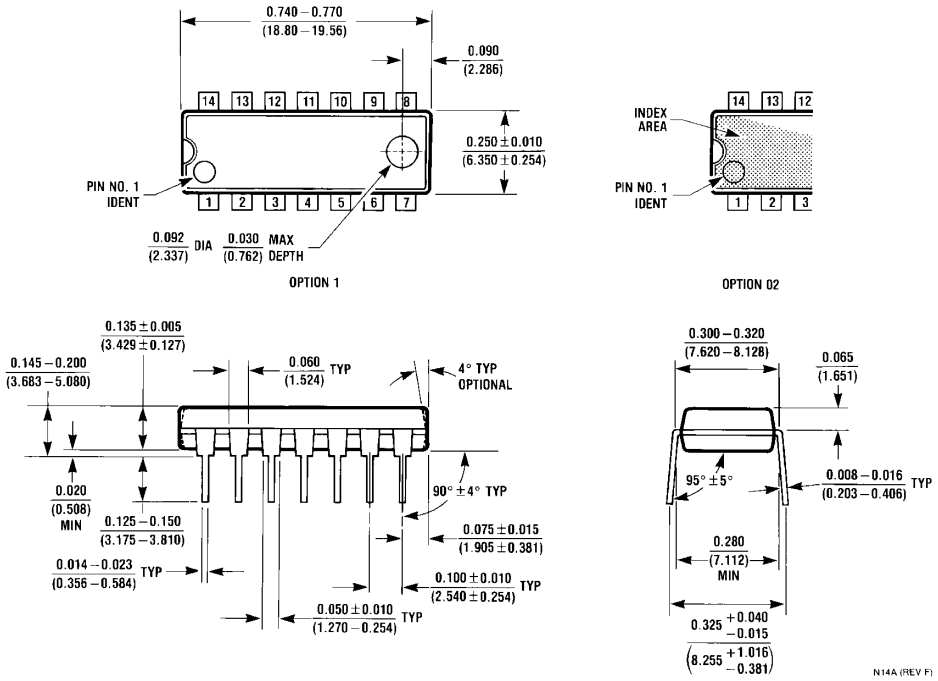
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

November 1992
Revised April 1999

74VHC86
Quad 2-Input Exclusive-OR Gate

General Description

The VHC86 is an advanced high speed CMOS Quad Exclusive OR Gate fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

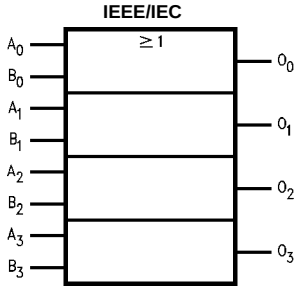
- High Speed: t_{PD} = 4.8 ns (typ) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 2 μA (Max.) @ T_A = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Power down protection is provided on all inputs
- Low Noise: V_{OLP} = 0.8V (Max.)
- Pin and Function Compatible with 74HC86

Ordering Code:

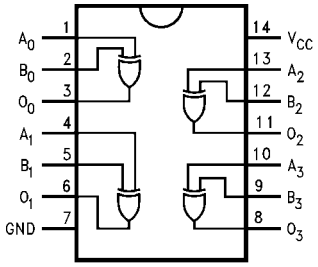
Order Number	Package Number	Package Description
74VHC86M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
74VHC86SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC86N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_0–A_3	Inputs
B_0–B_3	Inputs
O_0–O_3	Outputs

Truth Table

A	B	O
L	L	L
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ± 0.3V	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V		
		3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V		
		3.0 – 5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

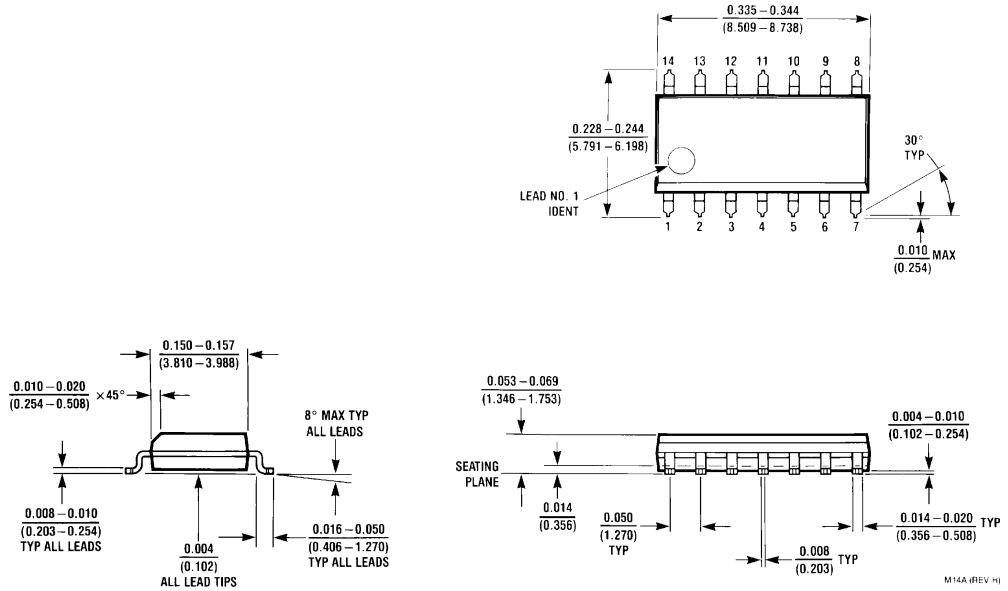
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

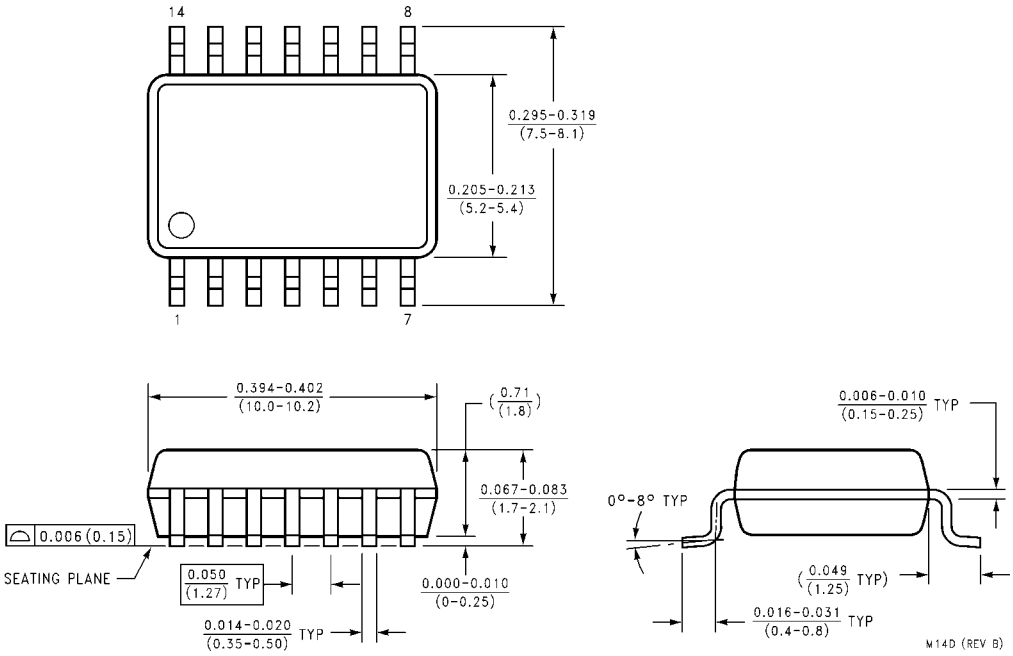
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL} t_{PLH}	Propagation Delay	3.3 ± 0.3		7.0	11.0	1.0	13.0	ns	$C_L = 15$ pF
				9.5	14.5	1.0	16.5		$C_L = 50$ pF
		5.0 ± 0.5		4.8	6.8	1.0	8.0	ns	$C_L = 15$ pF
				6.3	8.8	1.0	10.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

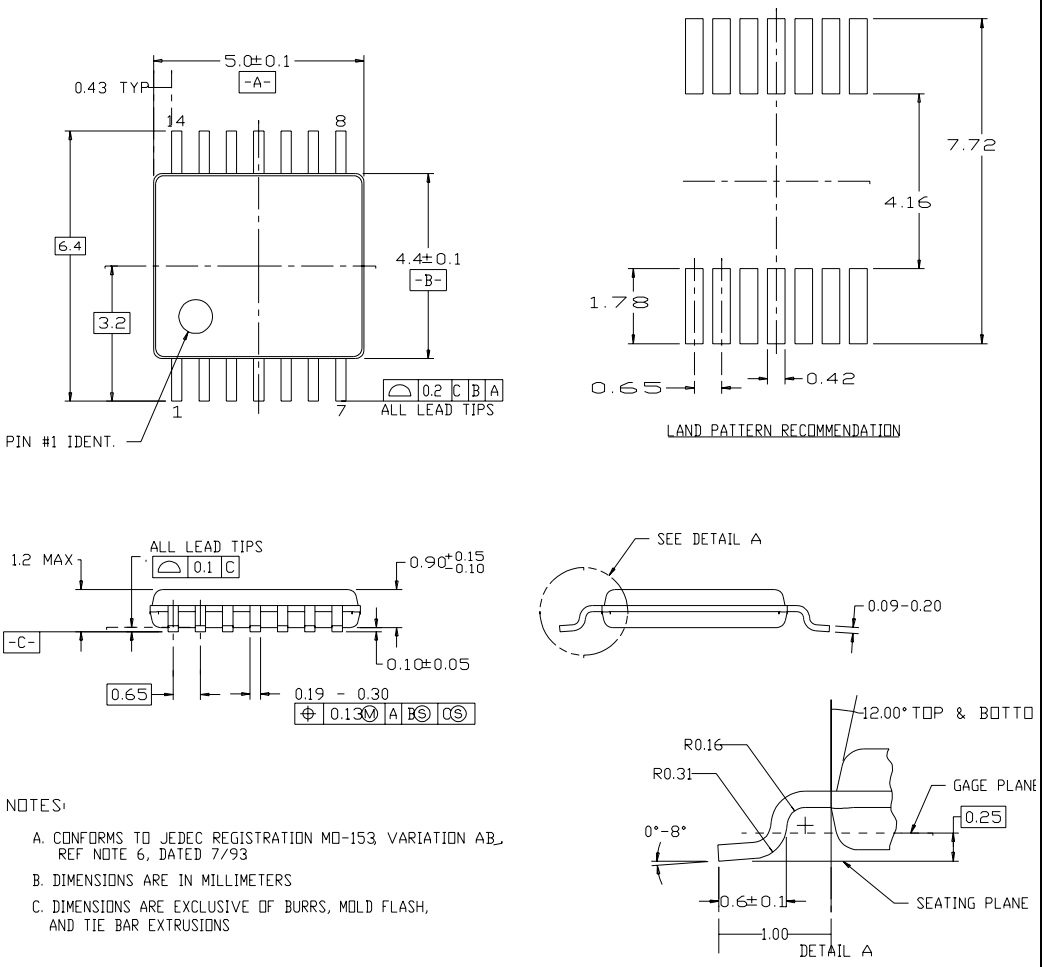


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

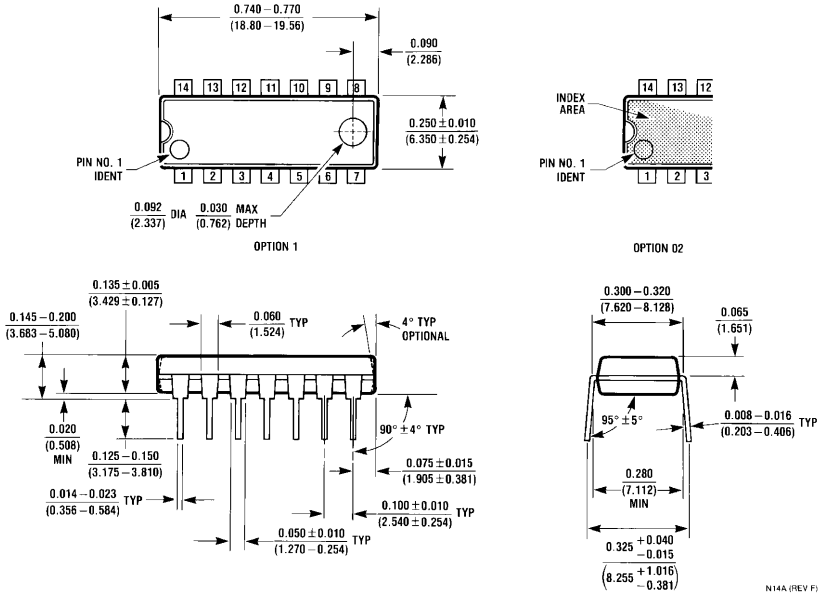
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

PRELIMINARY
October 1995

74VHC942 300 Baud Modem (+5V, −5V Supply)

General Description

The 74VHC942 is a full duplex low speed modem. It provides a 300 baud bidirectional serial interface for data communication over telephone lines and other narrow bandwidth channels. It is Bell 103 compatible.

The 74VHC942 utilizes advanced silicon-gate CMOS technology. Switched capacitor techniques are used to perform analog signal processing.

MODULATOR SECTION

The modulator contains a frequency synthesizer and a sine wave synthesizer. It produces a phase coherent frequency shift keyed (FSK) output.

LINE DRIVER AND HYBRID SECTION

The line driver and hybrid are designed to facilitate connection to a 600Ω phone line. They can perform two-to-four-wire conversion and drive the line at a maximum of 0 dBm.

DEMODULATOR SECTION

The demodulator incorporates anti-aliasing filters, a receive filter, limiter, discriminator, and carrier detect circuit. The nine pole receive filter provides 60 dB of transmitted tone rejection. The discriminator is fully balanced for stable operation.

Features

- ±5V supplies
- Drives 600Ω at 0 dBm
- All filters on chip
- Transmit level adjustment compatible with universal service order code
- TTL and CMOS compatible logic
- All inputs protected against static damage
- Low power consumption
- Full duplex answer or originate operation
- Analog loopback for self test
- Power down mode
- Direct pin and function replacement for the 74HC942

Applications

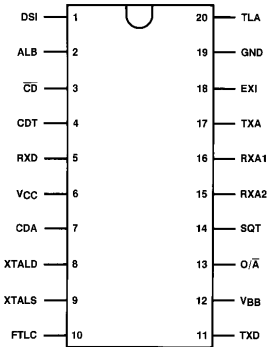
- Built-in low speed modems
- Remote data collection
- Radio telemetry
- Credit verification
- Stand-alone modems
- Point-of-sale terminals
- Tone signalling systems
- Remote process control

Commercial	Package Number	Package Description
74VHC942WM	M20B	20-Lead Molded JEDEC SOIC (0.300″ Wide)
74VHC942N	N20A	20-Lead Molded DIP

Note: Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignments for SOIC and PDIP



Top View

TL/F/11671–1

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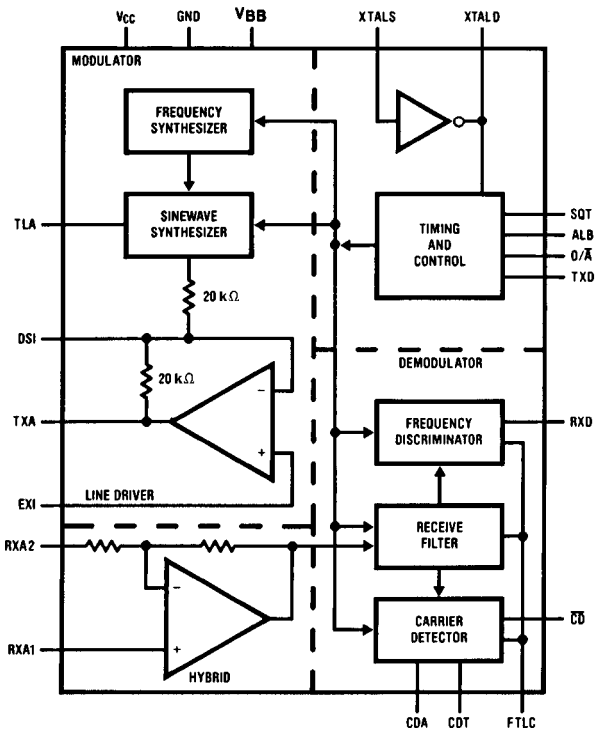
Block Diagram



TL/F/11671–2

Description of Pin Functions

Pin No.	Name	Function
1	DSI	Driver Summing Input: This may be used to transmit externally generated tones such as dual tone multifrequency (DTMF) dialing signals.
2	ALB	Analog Loop Back: A logic high on this pin causes the modulator output to be connected to the demodulator input so that data is looped back through the entire chip. This is used as a chip self test. If ALB and SQT are simultaneously held high the chip powers down.
3	$\overline{CD}$	Carrier Detect: This pin goes to a logic low when carrier is sensed by the carrier detect circuit.
4	CDT	Carrier Detect Timing: A capacitor on this pin sets the time interval that the carrier must be present before the $\overline{CD}$ goes low.
5	RXD	Received Data: This is the data output pin.
6	V_{CC}	Positive Supply Pin: A +5V supply is recommended.
7	CDA	Carrier Detect Adjust: This is used for adjustment of the carrier detect threshold. Carrier detect hysteresis is set at 3 dB.
8	XTALD	Crystal Drive: XTALD and XTALS connect to a 3.5795 MHz crystal to generate a crystal locked clock for the chip. If an external circuit requires this clock XTALD should be sensed. If a suitable clock is already available in the system, XTALD can be driven.
9	XTALS	Crystal Sense: Refer to Pin 8 for details.
10	FTLC	Filter Test/Limiter Capacitor: This is connected to a high impedance output of the receive filter. It may thus be used to evaluate filter performance. This pin may also be driven to evaluate the demodulator. RXA1 and RXA2 must be grounded during this test. For normal modem operation FTLC is AC grounded via a 0.1 μF bypass capacitor.
11	TXD	Transmitted Data: This is the data input.
12	V_{BB}	Negative Supply: The recommended supply is −5V.
13	O/$\overline{A}$	Originate/$\overline{Answer}$ mode select: When logic high this pin selects the originate mode of operation.
14	SQT	Squelch Transmitter: This disables the modulator when held high. The EXI input remains active. If SQT and ALB are simultaneously held high the chip powers down.
15	RXA2	Receive Analog #2: RXA2 and RXA1 are analog inputs. When connected as recommended they produce a 600Ω hybrid.
16	RXA1	Receive Analog #1: See RXA2 for details.
17	TXA	Transmit Analog: This is the output of the line driver.
18	EXI	External Input: This is a high impedance input to the line driver. This input may be used to transmit externally generated tones. When not used for this purpose it should be grounded.
19	GND	Ground: This defines the chip 0V.
20	TLA	Transmit Level Adjust: A resistor from this pin to V_{CC} sets the transmit level.

Functional Description

INTRODUCTION

A modem is a device for transmitting and receiving serial data over a narrow bandwidth communication channel. The 74VHC942 uses frequency shift keying (FSK) of an audio frequency tone. The tone may be transmitted over the switched telephone network and other voice grade channels. The 74VHC942 is also capable of demodulating FSK signals. By suitable tone allocation and considerable signal processing the 74VHC942 is capable of transmitting and receiving data simultaneously.

The tone allocation by the 74VHC942 and other Bell 103 compatible modems is shown in Table I. The terms ''originate'' and ''answer'' which define the frequency allocation come from use with telephones. The modem on the end of the line which initiates the call is called the originate modem. The other modem is the answer modem.

TABLE I. BELL 103 Allocation

Data	Originate Modem		Answer Modem	
	Transmit	Receive	Transmit	Receive
Space	1070 Hz	2025 Hz	2025 Hz	1070 Hz
Mark	1270 Hz	2225 Hz	2225 Hz	1270 Hz

THE LINE INTERFACE

The line interface section performs two to four wire conversion and provides impedance matching between the modem and the phone line.

THE LINE DRIVER

The line driver is a power amplifier for driving the line. If the modem is operating as an originate modem, the second harmonics of the transmitted tones fall close to the frequencies of the received tones and degrade the received signal to noise ratio (SNR). The line driver must thus produce low second harmonic distortion.

THE HYBRID

The voltage on the telephone line is the sum of the transmitted and received signals. The hybrid subtracts the transmitted voltage from the voltage on the telephone line. If the telephone line was matched to the hybrid impedance, the output of the hybrid would be only the received signal. This rarely happens because telephone line characteristic impedances vary considerably. The hybrid output is thus a mixture of transmitted and received signals.

THE DEMODULATOR SECTION

The Receive Filter

The demodulator recovers the data from the received signals. The signal from the hybrid is a mixture of transmitted signal, received signals and noise. The first stage of the receive filter is an anti-alias filter which attenuates high frequency noise before sampling occurs. The signal then goes to the second stage of the receive filter where the transmitted tones and other noise are filtered from the received signal. This is a switched capacitor nine-pole filter providing at least 60 dB of transmitted tone rejection. This also provides high attenuation at 60 Hz, a common noise component.

The Discriminator

The first stage of the discriminator is a hard limiter. The hard limiter removes from the received signal any amplitude modulation which may bias the demodulator toward a mark or a space. It compares the output of the receive filter to the voltage on the 0.1 μF capacitor on the FTLC pin.

The hard limiter output connects to two parallel bandpass filters in the discriminator. One filter is tuned to the mark frequency and the other to the space frequency. The outputs of these filters are rectified, filtered and compared. If the output of the mark path exceeds the output of the space path the RXD output goes high. The opposite case sends RXD low.

The demodulator is implemented using precision switched capacitor techniques. The highly critical comparators in the limiter and discriminator are auto-zeroed for low offset.

Carrier Detector

The output of the discriminator is meaningful only if there is sufficient carrier being received. This is established in the carrier detection circuit which measures the signal on the line. If this exceeds a certain level for a preset period (adjustable by the CDT pin) the $\overline{CD}$ output goes low indicating that carrier is present. Then the carrier detect threshold is lowered by 3 dB. This provides hysteresis ensuring the $\overline{CD}$ output remains stable. If carrier is lost $\overline{CD}$ goes high after the preset delay and the threshold is increased by 3 dB.

MODULATOR SECTION

The modulator consists of a frequency synthesizer and a sine wave synthesizer. The frequency produces one of four tones depending on the O/$\overline{A}$ and TXD pins. The frequencies are synthesized to high precision using a crystal oscillator and variable dual modulus counter. The counters used respond quickly to data changes, introducing negligible bit jitter while maintaining phase coherence.

The sine wave synthesizer uses switched capacitors to ''look up'' the voltages of the sine wave. This sampled signal is then further processed by switched capacitor and continuous filters to ensure the high spectral purity required by FCC regulations.

Absolute Maximum Ratings (Notes 1 & 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
Supply Voltage (V_{BB})	+0.5 to −7.0V
DC Input Voltage (V_{IN})	V_{BB} −1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	V_{BB} −0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.5	5.5	V
Supply Voltage (V_{BB})	−4.5	−5.5	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
74VHC	−40	+85	°C
Input Rise or Fall Times (t_r, t_f)		500	ns
Crystal frequency		3.579	MHz

DC Electrical Characteristics

Symbol	Parameter	Conditions	74VHC T = 25°C	74VHC T = −40 to 85°C	Units
			Typ	Guaranteed Limits	
V_{IH}	Minimum High Level Input Voltage			3.15	3.15	V
V_{IL}	Maximum Low Level Input Voltage			1.1	1.1	V
V_{OH}	Minimum High Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\|$ = 20 μA $\|I_{OUT}\|$ = 4.0 mA, V_{CC} = 4.5V	V_{CC}	V_{CC} −0.1 3.98	V_{CC} −0.1 3.7	V V
V_{OL}	Maximum Low Level Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\|$ = 20 μA $\|I_{OUT}\|$ = 4.0 mA, V_{CC} = 4.5V		0.1 0.26	0.1 0.4	V V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND		±0.1	±1.0	μA
I_{OZ}	Output TRI-STATE® Leakage Current RXD and $\overline{CD}$ Outputs	ALB = SQT = V_{CC}			±5	μA
I_{CC}, I_{BB}	Maximum Quiescent Supply Current	V_{IH} = V_{CC}, V_{IL} = GND ALB or SQT = GND Transmit Level = −9 dBm	8.0	12.0	12.0	mA
I_{CC}, I_{BB}	Power Down Supply Current	ALB = SQT = V_{CC} V_{IH} = V_{CC}, V_{IL} = GND			300	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

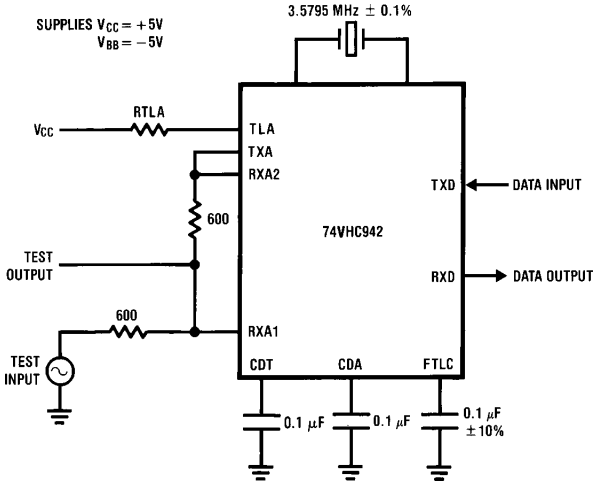
AC Electrical Characteristics

Unless otherwise specified, all specifications apply over the range −40°C to +85°C using a V_{CC} = +5V ±10%, a V_{BB} = −5V ±10% and a 3.579MHz ±0.1% crystal.*

Symbol	Parameter	Conditions		Min	Typ	Max	Units
TRANSMITTER							
F_{CE}	Carrier Frequency Error					4	Hz
	Power Output	V_{CC} = 5.0V	R_{TLA} = 0Ω	−3	−1.5	0	dBm
		R_L = 1.2 kΩ	R_{TLA} = 5.49 kΩ	−12	−10.5	−9	dBm
	2nd Harmonic Energy		R_{TLA} = 0Ω		−62	−56	dBm
RECEIVE FILTER AND HYBRID							
	Hybrid Input Impedance (Pins 15 and 16)			50			kΩ
	FTLC Output Impedance			5	10	50	kΩ
	Adjacent Channel Rejection	RXA2 = GND TXA = GND or V_{CC} Input to RXA1		60			dB
DEMODULATOR (INCORPORATING HYBRID, RECEIVE FILTER AND DISCRIMINATOR)							
	Carrier Amplitude			−38		−9	dBm
	Bit Jitter	SNR = 30 dB Input = −38 dBm Baud Rate = 300 Baud			100	200	μS
	Bit Bias	Alternating 1-0 Pattern			5	10	%
	Carrier Detect Trip Points	CDA = 1.2V	Off to On	−38	−37	−34	dBm
		V_{CC} = 5.0V	On to Off	−41	−40	−37	dBm
	Carrier Detect Hysteresis	V_{CC} = 5V		2	3	4	dB

*The demodulator specifications apply to the 74VHC942 operating with a modulator having frequency accuracy, phase jitter and harmonic content equal to or better than the 74VHC942 modulator.

AC Specification Circuit



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Applications Information

TRANSMIT LEVEL ADJUSTMENT

The transmitted power levels of Table II refer to the power delivered to a 600Ω load from the external 600Ω source impedance. The voltage on the load is half the TXA voltage. This should be kept in mind when designing interface circuits which do not match the load and source impedances.

The transmit level is programmable by placing a resistor from TLA to VCC. With a 5.5k resistor the line driver transmits a maximum of −9 dBm. Since most lines from a phone installation to the exchange provide 3 dB of attenuation the maximum level reaching the exchange will be −12 dBm. This is the maximum level permitted by most telephone companies. Thus with this programming the 74VHC942 will interface to most telephones. This arrangement is called the ''permissive arrangement.'' The disadvantage with the permissive arrangement is that when the loss from a phone to the exchange exceeds 3 dB, no compensation is made and SNR may be unnecessarily degraded.

SNR can be maximized by adjusting the transmit level until the level at the exchange reaches −12 dBm. This must be done with the cooperation of the telephone company. The programming resistor used is specific for a given installation and is often included in the telephone jack at the installation. The modem is thus programmable and can be used with any jack correctly wired. This arrangement is called the universal registered jack arrangement and is possible with the 74VHC942. The values of resistors required to program the 74VHC942 follow the most common code in use; the universal service order code. The required resistors are given in Table II.

TABLE II. Universal Service Order Code Resistor Values

Line Loss (dB)	Transmit Level (dBm)	Programming Resistor (R_{TLA}) (Ohms)
0	−12	Open
1	−11	19,800
2	−10	9,200
3	−9	5,490
4	−8	3,610
5	−7	2,520
6	−6	1,780
7	−5	1,240
8	−4	866
9	−3	562
10	−2	336
11	−1	150
12	0	0

CARRIER DETECT THRESHOLD ADJUSTMENT

The carrier detect threshold is directly proportional to the voltage on CDA. This pin is connected internally to a high impedance source. This source has a nominal Thevenin equivalent voltage of 1.2V and output impedance of 100 kΩ.

By forcing the voltage on CDA the carrier detect threshold may be adjusted. To find the voltage required for a given threshold the following equation may be used;

$$V_{CDA} = 244 \times V_{ON}$$

$$V_{CDA} = 345 \times V_{OFF}$$

CARRIER DETECT TIMING ADJUSTMENT

CDT: A capacitor on Pin 4 sets the time interval that the carrier must be present before $\overline{CD}$ goes low. It also sets the time interval that carrier must be removed before $\overline{CD}$ returns high. The relevant timing equations are:

$T_{\overline{CD}L} \cong 6.4 \times C_{CDT}$ for $\overline{CD}$ going low

$T_{\overline{CD}H} \cong 0.54 \times C_{CDT}$ for $\overline{CD}$ going high

Where $T_{\overline{CD}L}$ & $T_{\overline{CD}H}$ are in seconds, and C_{CDT} is in μF.

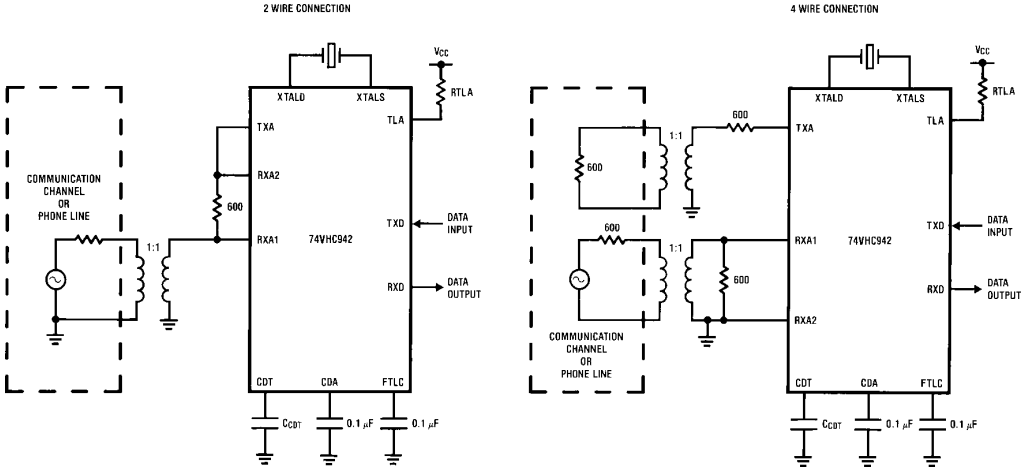
DESIGN PRECAUTIONS

Power supplies to digital systems may contain high amplitude spikes and other noise. To optimize performance of the 74VHC942 operating in close proximity to digital systems, supply and ground noise should be minimized. This involves attention to power supply design and circuit board layout.

Power supply decoupling close to the device is recommended. Ground loops should be avoided. For further discussion of these subjects see the Audio/Radio Handbook published by National Semiconductor Corporation.

Applications Information (Continued)

Interface Circuits for 74VHC942 300 Baud Modem



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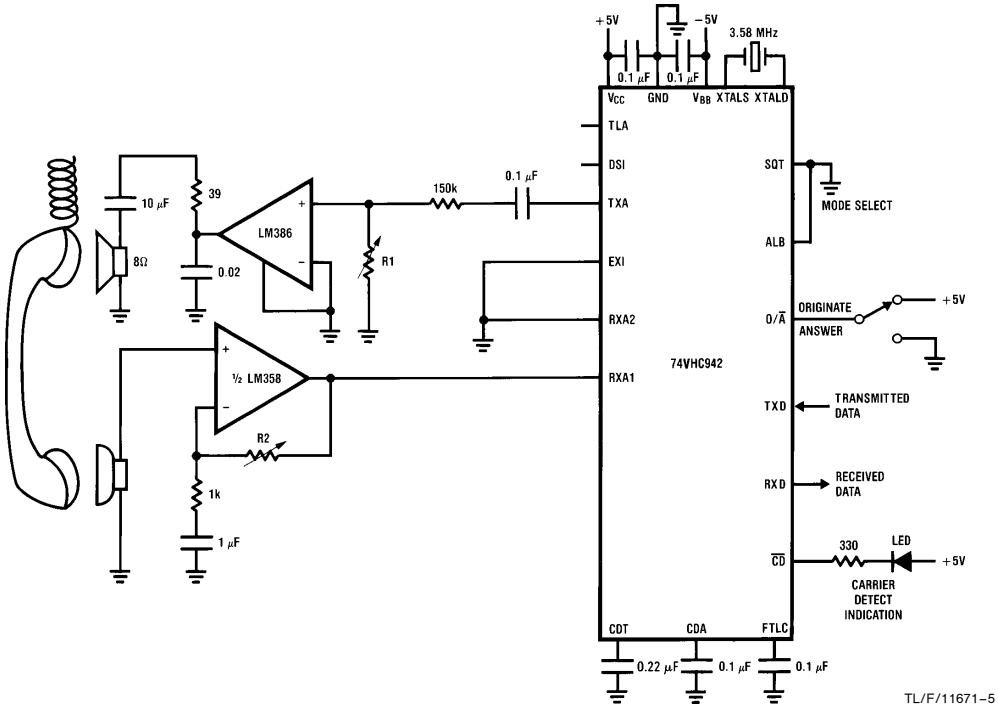
C_{CDT} and R_{TLA} should be chosen to suit the application.

Complete Acoustically Coupled 300 Baud Modem



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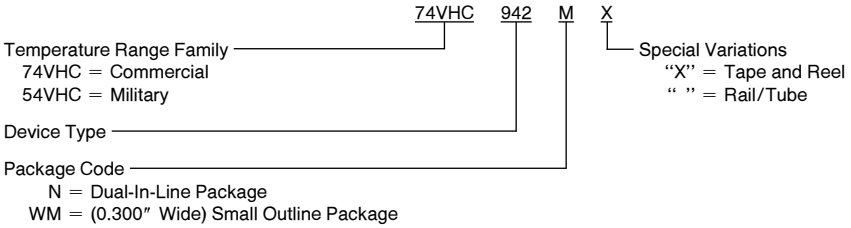
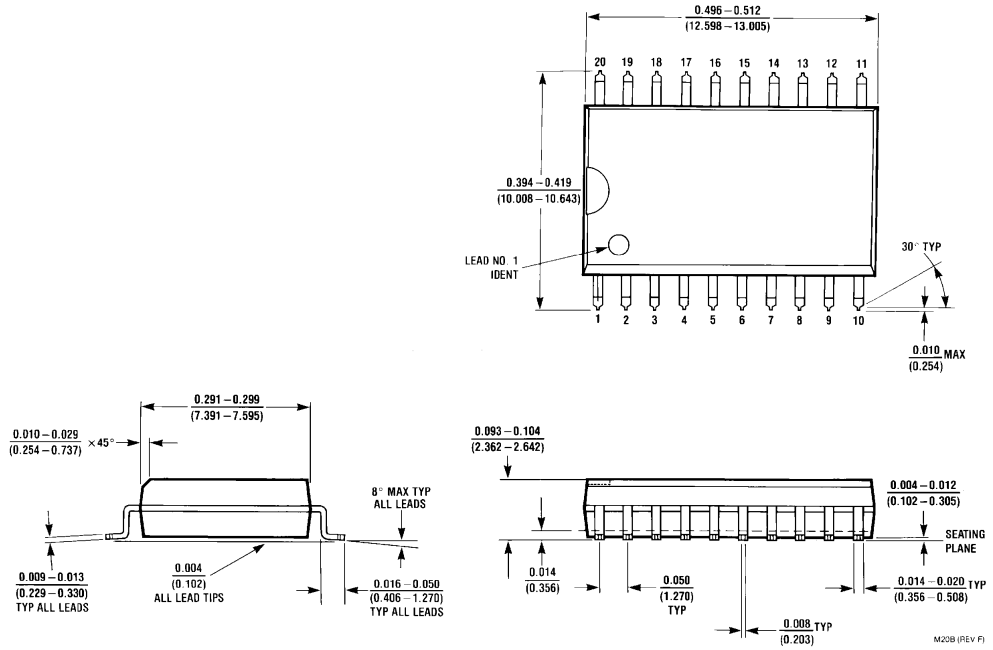
Note: The efficiency of the acoustic coupling will set the valves of R1 and R2.

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

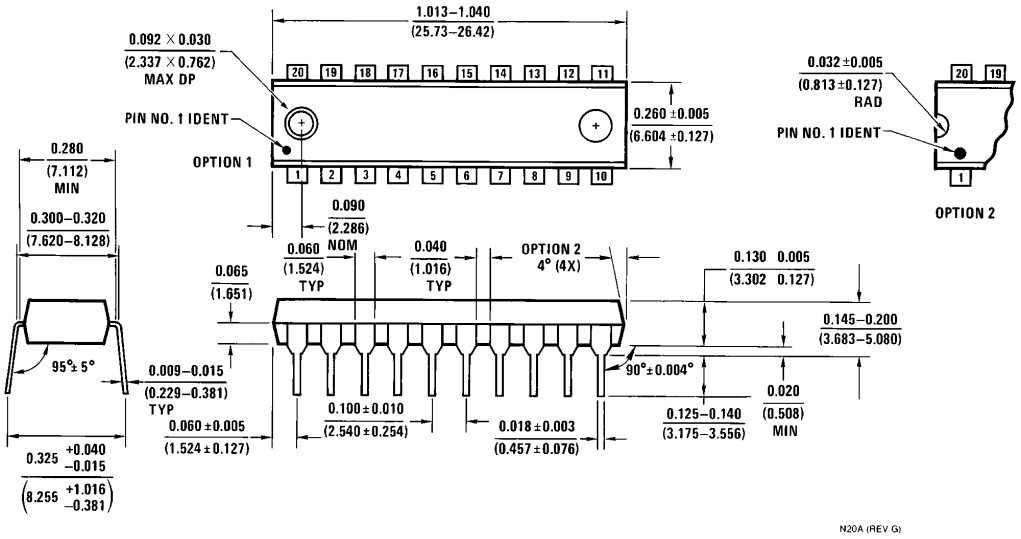


Physical Dimensions inches (millimeters)



20-Lead (0.300″ Wide) Molded Small Outline Package JEDEC
Order Number 74VHC942WM
NS Package Number M20B

Physical Dimensions inches (millimeters) (Continued)



20-Lead (0.300″ Wide) Molded Dual-In-Line Package
Order Number 74VHC942N
NS Package Number N20A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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National Semiconductor

PRELIMINARY
October 1995

74VHC943
300 Baud Modem (5V Supply)

General Description

The 74VHC943 is a full duplex low speed modem. It provides a 300 baud bidirectional serial interface for data communication over telephone lines and other narrow bandwidth channels. It is Bell 103 compatible.

The 74VHC943 utilizes advanced silicon-gate CMOS technology. Switched capacitor techniques are used to perform analog signal processing.

MODULATOR SECTION

The modulator contains a frequency synthesizer and a sine wave synthesizer. It produces a phase coherent frequency shift keyed (FSK) output.

LINE DRIVER AND HYBRID SECTION

The line driver and hybrid are designed to facilitate connection to a 600Ω phone line. They can perform two to four wire conversion and drive the line at a maximum of −9 dBm.

DEMODULATOR SECTION

The demodulator incorporates anti-aliasing filters, a receive filter, limiter, discriminator, and carrier detect circuit. The nine-pole receive filter provides 60 dB of transmitted tone rejection. The discriminator is fully balanced for stable operation.

Features

- 5V supply
- Drives 600Ω at −9 dBm
- All filters on chip
- Transmit level adjustment compatible with universal service order code
- TTL and CMOS compatible logic
- All inputs protected against static damage
- Low power consumption
- Full duplex answer or originate operation
- Analog loopback for self test
- Power down mode
- Direct Pin and function replacement for the 74HC943

Applications

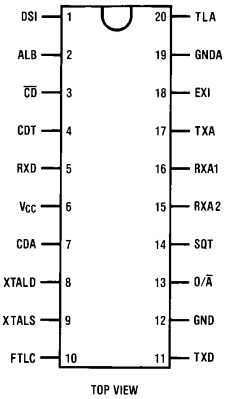
- Built-in low speed modems
- Remote data collection
- Radio telemetry
- Credit verification
- Stand-alone modems
- Point-of-sale terminals
- Tone signaling systems
- Remote process control

Commercial	Package Number	Package Description
74VHC943WM	M20B	20-Lead Molded JEDEC SOIC (0.300″ Wide)
74VHC943N	N20A	20-Lead Molded DIP

Note: Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignments for SOIC and PDIP



TOP VIEW

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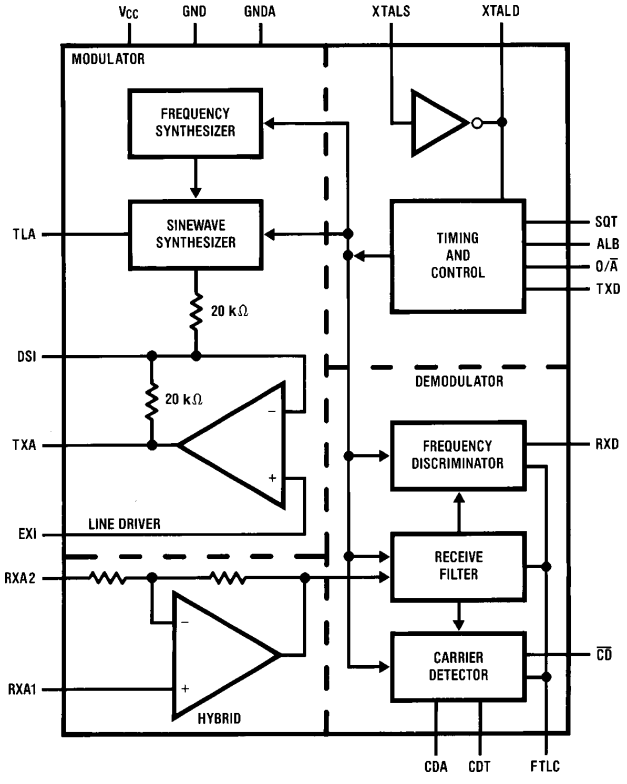
Block Diagram



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Description of Pin Functions

Pin No.	Name	Function
1	DSI	Driver Summing Input: This input may be used to transmit externally generated tones such as dual tone multifrequency (DTMF) dialing signals.
2	ALB	Analog Loop Back: A logic high on this pin causes the modulator output to be connected to the demodulator input so that data is looped back through the entire chip. This is used as a chip self test. If ALB and SQT are simultaneously held high the chip powers down.
3	$\overline{CD}$	Carrier Detect: This pin goes to a logic low when carrier is sensed by the carrier detect circuit.
4	CDT	Carrier Detect Timing: A capacitor on this pin sets the time interval that the carrier must be present before the $\overline{CD}$ goes low.
5	RXD	Received Data: This is the data output pin.
6	V_{CC}	Positive Supply Pin: A +5V supply is recommended.
7	CDA	Carrier Detect Adjust: This is used for adjustment of the carrier detect threshold. Carrier detect hysteresis is set at 3 dB.
8	XTALD	Crystal Drive: XTALD and XTALS connect to a 3.5795 MHz crystal to generate a crystal locked clock for the chip. If an external circuit requires this clock XTALD should be sensed. If a suitable clock is already available in the system. XTALD can be driven.
9	XTALS	Crystal Sense: Refer to pin 8 for details.
10	FTLC	Filter Test/Limiter Capacitor: This is connected to a high impedance output of the receiver filter. It may thus be used to evaluate filter performance. This pin may also be driven to evaluate the demodulator. RXA1 and RXA2 must be grounded during this test. For normal modem operation FTLC is AC grounded via a 0.1 μF bypass capacitor.
11	TXD	Transmitted Data: This is the data input.
12	GND	Ground: This defines the chip 0V.
13	O/$\overline{A}$	Originate/$\overline{Answer}$ mode select: When logic high this pin selects the originate mode of operation.
14	SQT	Squelch Transmitter: This disables the modulator when held high. The EXI input remains active. If SQT and ALB are simultaneously held high the chip powers down.
15	RXA2	Receive Analog #2: RXA2 and RXA1 are analog inputs. When connected as recommended they produce a 600Ω hybrid.
16	RXA1	Receive Analog #1: See RXA2 for details.
17	TXA	Transmit Analog: This is the output of the line driver.
18	EXI	External Input: This is a high impedance input to the line driver. This input may be used to transmit externally generated tones. When not used for this purpose it should be grounded to GNDA.
19	GNDA	Analog Ground: Analog signals within the chip are referred to this pin.
20	TLA	Transmit Level Adjust: A resistor from this pin to V_{CC} sets the transmit level.

Functional Description

INTRODUCTION

A modem is a device for transmitting and receiving serial data over a narrow bandwidth communication channel. The 74VHC943 uses frequency shift keying (FSK) of audio frequency tone. The tone may be transmitted over the switched telephone network and other voice grade channels. The 74VHC943 is also capable of demodulating FSK signals. By suitable tone allocation and considerable signal processing the 74VHC943 is capable of transmitting and receiving data simultaneously.

The tone allocation used by the 74VHC943 and other Bell 103 compatible modems is shown in Table I. The terms ''originate'' and ''answer'' which define the frequency allocation come from use with telephones. The modem on the end of the line which initiates the call is called the originate modem. The other modem is the answer modem.

TABLE I. Bell 103 Tone Allocation

Data	Originate Modem		Answer Modem	
	Transmit	Receive	Transmit	Receive
Space	1070 Hz	2025 Hz	2025 Hz	1070 Hz
Mark	1270 Hz	2225 Hz	2225 Hz	1270 Hz

THE LINE INTERFACE

The line interface section performs two to four wire conversion and provides impedance matching between the modem and the phone line.

THE LINE DRIVER

The line driver is a power amplifier for driving the line. If the modem is operating as an originate modem, the second harmonics of the transmitted tones fall close to the frequencies of the received tones and degrade the received signal to noise ratio (SNR). The line driver must thus produce low second harmonic distortion.

THE HYBRID

The voltage on the telephone line is the sum of the transmitted and received signals. The hybrid subtracts the transmitted voltage from the voltage on the telephone line. If the telephone line was matched to the hybrid impedance, the output of the hybrid would be only the received signal. This rarely happens because telephone line characteristic impedances vary considerably. The hybrid output is thus a mixture of transmitted and received signals.

THE DEMODULATOR SECTION

The Receive Filter

The demodulator recovers the data from the received signals. The signal from the hybrid is a mixture of transmitted signal, received signals and noise. The first stage of the receive filter is an anti-alias filter which attenuates high frequency noise before sampling occurs. The signal then goes to the second stage of the receive filter where the transmitted tones and other noise are filtered from the received signal. This is a switch capacitor nine pole filter providing at least 60 dB of transmitted tone rejection. This also provides high attenuation at 60 Hz, a common noise component.

The Discriminator

The first stage of the discriminator is a hard limiter. The hard limiter removes from the received signal any amplitude modulation which may bias the demodulator toward a mark or a space. It compares the output of the receive filter to the voltage on the 0.1 μF capacitor on the FTLC pin.

The hard limiter output connects to two parallel bandpass filters in the discriminator. One filter is tuned to the mark frequency and the other to the space frequency. The outputs of these filters are rectified, filtered and compared. If the output of the mark path exceeds the output of the space path the RXD output goes high. The opposite case sends RXD low.

The demodulator is implemented using precision switched capacitor techniques The highly critical comparators in the limiter and discriminator are auto-zeroed for low offset.

Carrier Detector

The output of the discriminator is meaningful only if there is sufficient carrier being received. This is established in the carrier detection circuit which measures the signal on the line. If this exceeds a certain level for a preset period (adjustable by the CDT pin) the $\overline{CD}$ output goes low indicating that carrier is present. Then the carrier detect threshold is lowered by 3 dB. This provides hysteresis ensuring the $\overline{CD}$ output remains stable. If carrier is lost $\overline{CD}$ goes high after the preset delay and the threshold is increased by 3 dB.

MODULATOR SECTION

The modulator consists of a frequency synthesizer and a sine wave synthesizer. The frequency synthesizer produces one of four tones depending on the O/$\overline{A}$ and TXD pins. The frequencies are synthesized to high precision using a crystal oscillator and variable dual modulus counter.

The counters used respond quickly to data changes, introducing negligible bit jitter while maintaining phase coherence.

The sine wave synthesizer uses switched capacitors to ''look up'' the voltages of the sine wave. This sampled signal is then further processed by switched capacitor and continuous filters to ensure the high spectral purity required by FCC regulations.

Absolute Maximum Ratings (Notes 1 & 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.5	5.5	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
74VHC	−40	+85	°C
Input Rise or Fall Times (t_r, t_f)		500	ns
Crystal frequency		3.579	MHz

DC Electrical Characteristics V_{CC} = 5V ±10% unless otherwise specified

Symbol	Parameter	Conditions	74VHC T_A = 25°C		74VHC T_A = −40°C to +85°C	Units
			Typ	Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage			3.15	3.15	V
V_{IL}	Maximum Low Level Input Voltage			1.1	1.1	V
V_{OH}	Minimum High Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\|$ = 20 μA $\|I_{OUT}\|$ = 4.0 mA, V_{CC} = 4.5V	V_{CC} −0.05	V_{CC} −0.1 3.84	V_{CC} −0.1 3.7	V
V_{OL}	Maximum Low Level Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\|$ = 20 μA $\|I_{OUT}\|$ = 4.0 mA, V_{CC} = 4.5V		0.1 0.33	0.1 0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND		±0.1	±1.0	μA
I_{OZ}	Output TRI-STATE® Leakage Current, RXD and $\overline{CD}$ Outputs	ALB = SQT = V_{CC}			±5	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IH} = V_{CC}, V_{IL} = GND ALB or SQT = GND Transmit Level = −9 dBm	8.0	10.0	10.0	mA
I_{GNDA}	Analog Ground Current		1.0	2.0	2.0	mA
I_{CC}	Power Down Supply Current	ALB = SQT = V_{CC} V_{IH} = V_{CC}, V_{IL} = GND			300	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

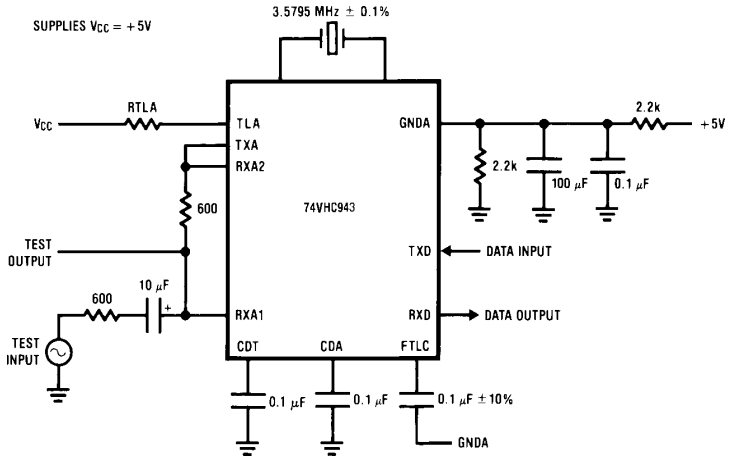
AC Electrical Characteristics

Unless otherwise specified, all specifications apply over the range −40°C to +85°C using a V_{CC} of +5V ±10%, and a 3.579 MHz ±0.1% crystal*

Symbol	Parameter	Conditions		Min	Typ	Max	Units
TRANSMITTER							
F_{CE}	Carrier Frequency Error					4	Hz
	Power Output	V_{CC} = 5.0V R_L = 1.2 kΩ	R_{TLA} = 5490Ω	−12	−10.5	−9	dBm
	2nd Harmonic Energy		R_{TLA} = 5490Ω		−62	−56	dBm
RECEIVE FILTER AND HYBRID							
	Hybrid Input Impedance (Pins 15 and 16)			50			kΩ
	FTLC Output Impedance			5	10	50	kΩ
	Adjacent Channel Rejection	RXA2 = GNDA, TXD = GND or V_{CC} Input to RXA1		60			dB
DEMODULATOR (INCORPORATING HYBRID, RECEIVE FILTER AND DISCRIMINATOR)							
	Carrier Amplitude			−38		−12	dBm
	Bit Jitter	SNR = 30 dB Input = −38 dBm Baud Rate = 300 Baud			100	200	μs
	Bit Bias	Alternating 1–0 Pattern			5	10	%
	Carrier Detect Trip Points	CDA = 1.2V	Off to On	−38	−36	−34	dBm
		V_{CC} = 5.0V	On to Off	−41	−39	−37	dBm
	Carrier Detect Hystereisis	V_{CC} = 5.0V		2	3	4	dB

*The demodulator specifications apply to the 74VHC943 operating with a modulator having frequency accuracy, phase jitter and harmonic content equal to or better than the 74VHC943 modulator.

AC Specification Circuit



TL/F/11679–3

Applications Information

TRANSMIT LEVEL ADJUSTMENT

The transmitted power levels of Table II refer to the power delivered to a 600Ω load from the external 600Ω source impedance. The voltage on the load is half the TXA voltage. This should be kept in mind when designing interface circuits which do not match the load and source inpedances.

The transmit level is programmable by placing a resistor from TLA to V_{CC}. With a 5.5k resistor the line driver transmits a maximum of −9 dBm. Since most lines from a phone installation to the exchange provide 3 dB of attenuation the maximum level reaching the exchange will be −12 dBm. This is the maximum level permitted by most telephone companies. Thus with this programming the 74VHC943 will interface to most telephones. This arrangement is called the ''permissive arrangement.'' The disadvantage with the permissive arrangement is that when the loss from a phone to the exchange exceeds 3 dB, no compensation is made and SNR may be unnecessarily degraded.

TABLE II. Universal Service Order Code Resistor Values

Line Loss (dB)	Transmit Level (dBm)	Programming Resistor (R_{TLA}) (Ω)
0	−12	Open
1	−11	19,800
2	−10	9,200
3	−9	5,490

CARRIER DETECT THRESHOLD ADJUSTMENT

The carrier detect threshold is directly proportional to the voltage on CDA. This pin is connected internally to a high impedance source. This source has a nominal Thevenin equivalent voltage of 1.2V and output impedance of 100 kΩ.

By forcing the voltage on CDA the carrier detect threshold may be adjusted. To find the voltage required for a given threshold the following equation may be used:

$$V_{CDA} = 244 \times V_{ON}$$

$$V_{CDA} = 345 \times V_{OFF}$$

CARRIER DETECT TIMING ADJUSTMENT

CDT: A capacitor on Pin 4 sets the time interval that the carrier must be present before $\overline{CD}$ goes low. It also sets the time interval that carrier must be removed before $\overline{CD}$ returns high. The relevant timing equations are:

$$T_{\overline{CDL}} \cong 6.4 \times C_{CDT} \quad \text{for } \overline{CD} \text{ going low}$$

$$T_{\overline{CDH}} \cong 0.54 \times C_{CDT} \quad \text{for } \overline{CD} \text{ going high}$$

Where $T_{\overline{CDL}}$ & $T_{\overline{CDH}}$ are in seconds, and C_{CDT} is in μF.

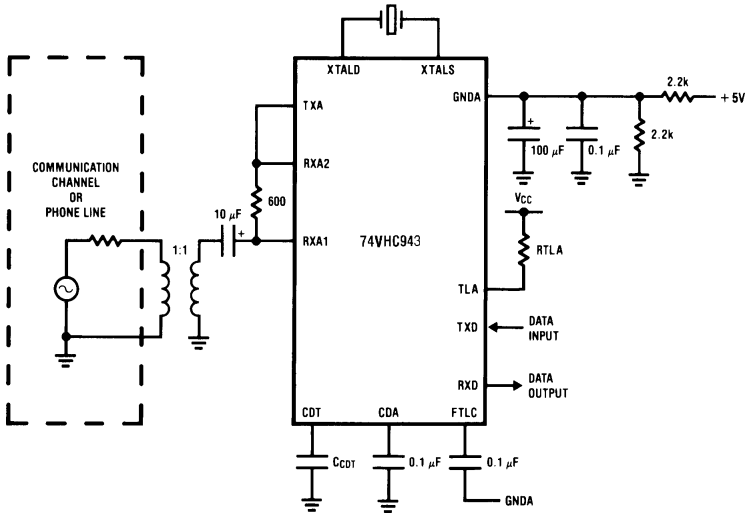
DESIGN PRECAUTIONS

Power supplies to digital systems may contain high amplitude spikes and other noise. To optimize performance of the 74VHC943 operating in close proximity to digital systems, supply and ground noise should be minimized. This involves attention to power supply design and circuit board layout. Power supply decoupling close to the device is recommended. Ground loops should be avoided. For further discussion of these subjects see the Audio/Radio Handbook published by National Semiconductor Corporation.

Applications Information (Continued)

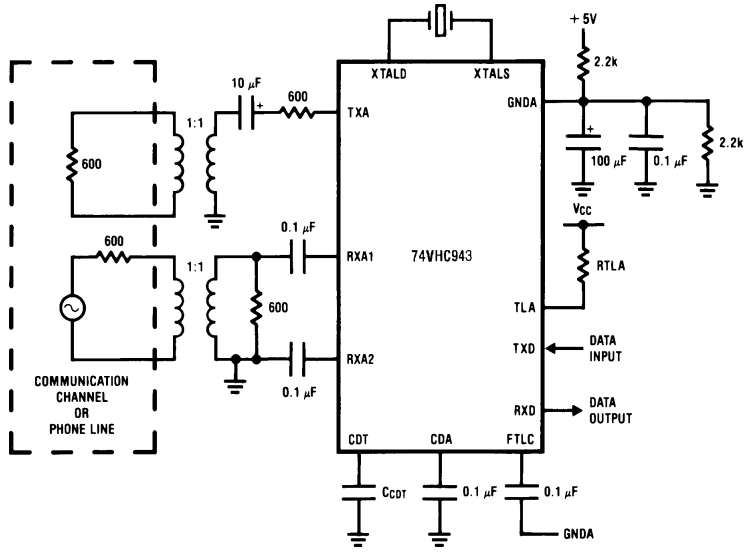
Interface Circuits for 74VHC943 300 Baud Modem

2 Wire Connection



TL/F/11679–4

4 Wire Connection

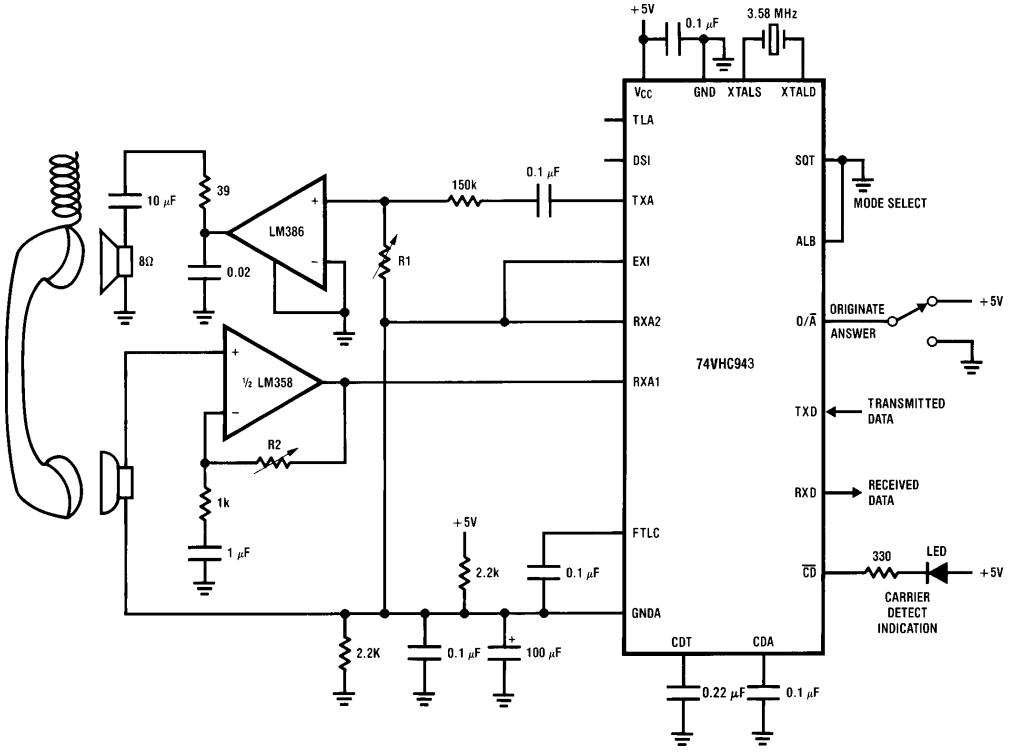


TL/F/11679–5

C_{CDT} and R_{TLA} should be chosen to suit the application. See the Applications Information for more details.

Applications Information (Continued)

Complete Acoustically Coupled 300 Baud Modem

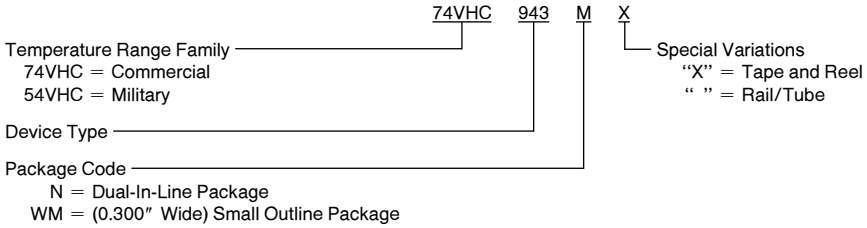


TL/F/11679–6

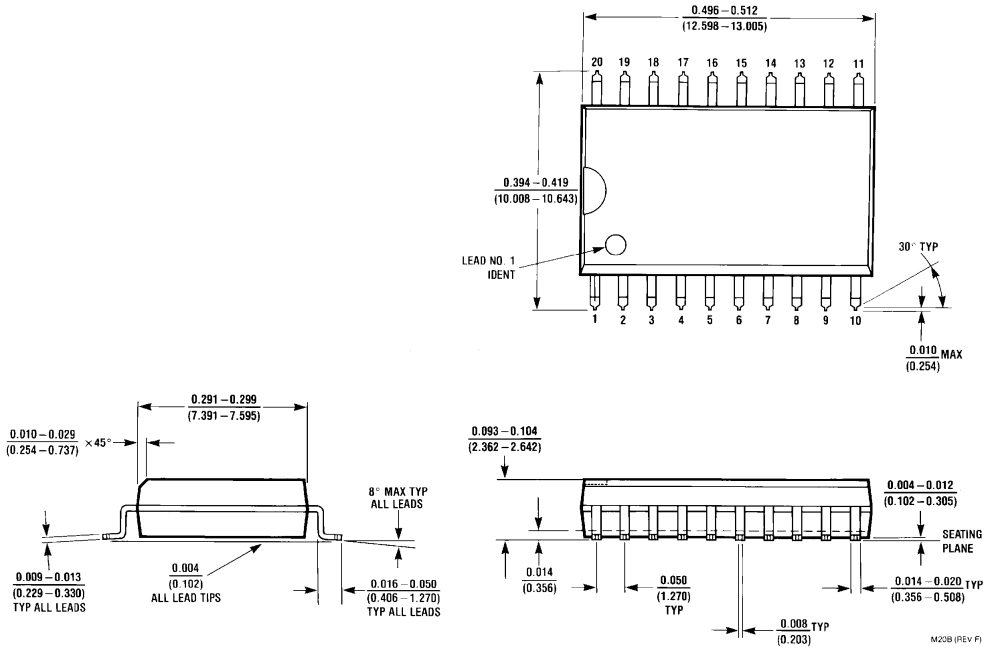
Note: The efficiency of the acoustic coupling will set the values of R1 and R2.

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

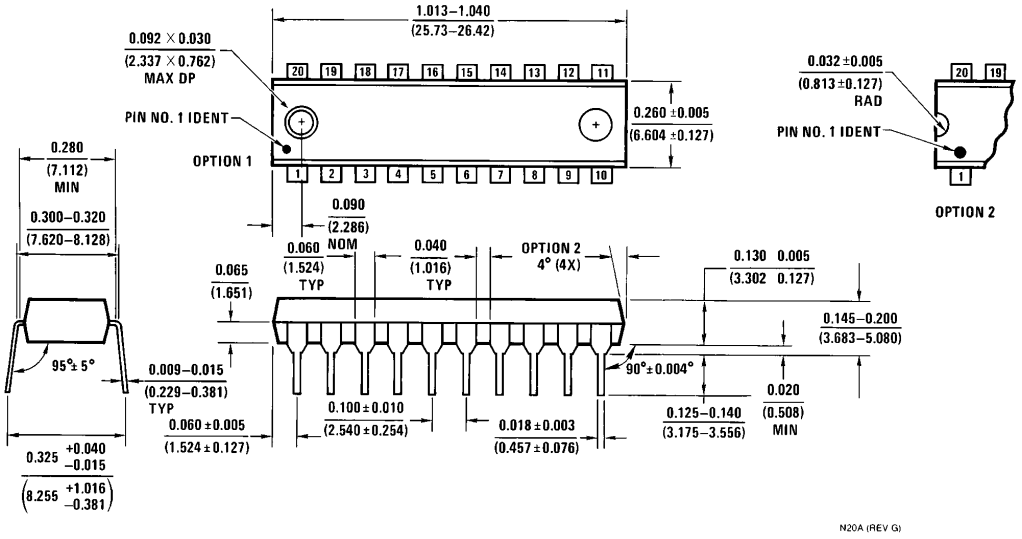


Physical Dimensions inches (millimeters)



20-Lead (0.300″ Wide) Molded Small Outline Package JEDEC
Order Number 74VHC943WM
NS Package Number M20B

Physical Dimensions inches (millimeters) (Continued)



20-Lead (0.300″ Wide) Molded Dual-In-Line Package
Order Number 74VHC943N
NS Package Number N20A

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FAIRCHILD SEMICONDUCTOR™

February 1998

74VHC00 • 74VHCT00
Quad 2-Input NAND Gate

General Description

The VHC/VHCT00 is an advanced high-speed CMOS 2-Input NAND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC t_{pd} = 3.7ns (typ) at T_A = 25˚C
  VHCT t_{pd} = 5.0 ns (typ) at T_A= 25˚C
- High noise immunity:
  VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection:
  VHC inputs only
  VHCT inputs and outputs
- Low noise: V_{OLP} = 0.8V (max)
- Low power dissipation:
  I_{CC} = 2 µA (max) at T_A = 25˚C
- Pin and function compatible with 74HC/HCT00
  NOTE: ADD EXTERNAL PULL UP RESISTOR TO VHCT OUTPUTS TO DRIVE CMOS INPUTS

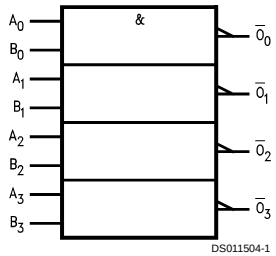
Ordering Code:

Commercial	Package Number	Package Description
74VHC00M	M14A	14-Lead Molded JEDEC SOIC
74VHC00SJ	M14D	14-Lead Molded EIAJ SOIC
74VHC00MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHC00N	N14A	14-Lead Molded DIP
74VHCT00M	M14A	14-Lead Molded JEDEC SOIC
74VHCT00SJ	M14D	14-Lead Molded EIAJ SOIC
74VHCT00MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHCT00N	N14A	14-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X' to the ordering code.

Logic Symbol

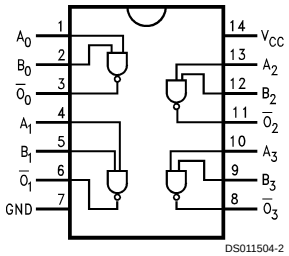
IEEE/IEC



DS011504-1

Connection Diagram

Pin Assignment for DIP,TSSOP and SOIC



DS011504-2

Pin Descriptions

Pin Names	Description
An, Bn	Inputs
On	Outputs

Truth Table

A	B	O
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} +0.5V
VHCT (Note 2)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260˚C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to +5.5V
VHCT	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC Only)	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: $V_{OUT} > V_{CC}$ only if output is in H state.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4mA
		4.5	3.94			3.80				I_{OH} = −8mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}, t_{PHL}	Propagation Delay	3.3 ±0.3		5.5	7.9	1.0	9.5	ns	C_L = 15 pF
				8.0	11.4	1.0	13.0		C_L = 50 pF
		5.0 ±0.5		3.7	5.5	1.0	6.5	ns	C_L = 15 pF
				5.2	7.5	1.0	8.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 5)

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH}	I_{OH} = −50 µA
		4.5	2.5			2.4		V		I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 µA
		4.5			0.36		0.44	V		I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/ Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	µA	V_{OUT} = 5.5V	

Noise Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 6)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 6)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 6)	Minimum High Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 6)	Maximum Low Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

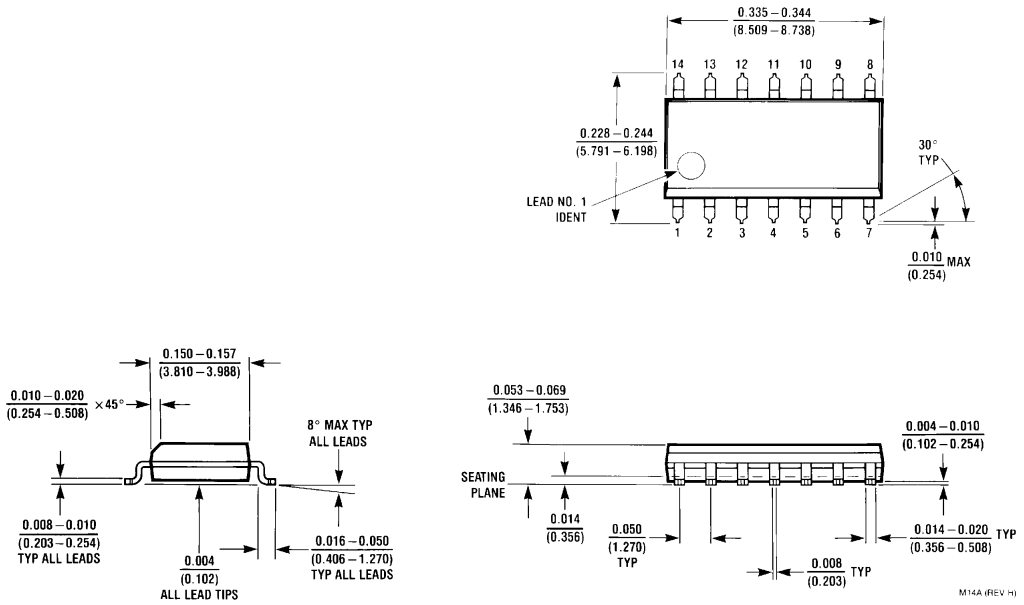
Note 6: Parameter guaranteed by design.

AC Electrical Characteristics for VHCT

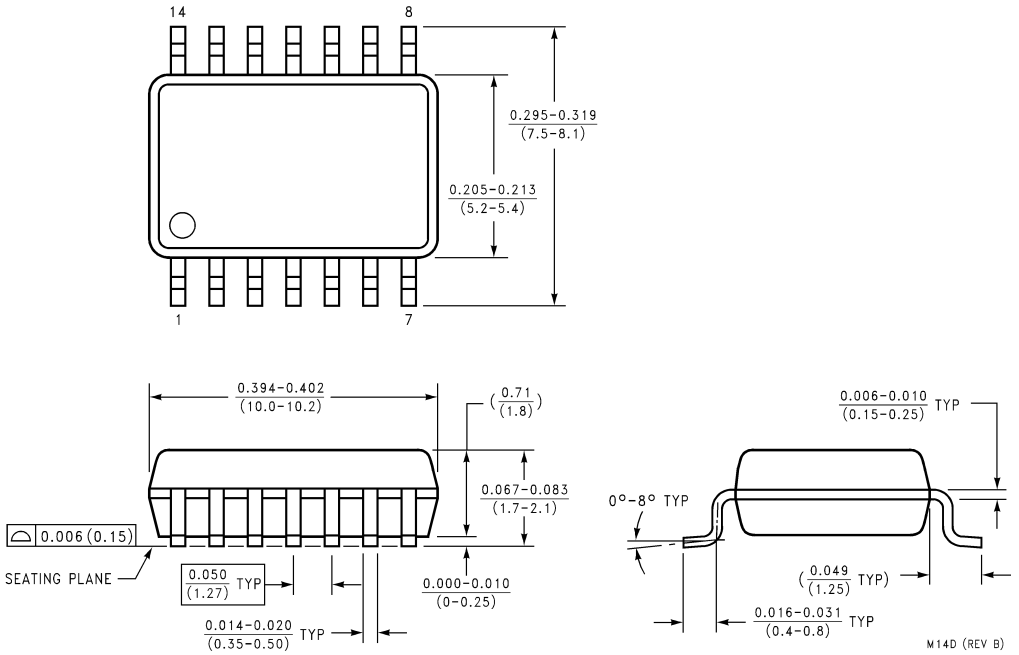
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	Fig. No.
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0		5.0	6.9	1.0	8.0	ns	C_L = 15 pF	
t_{PHL}		±0.5		5.5	7.9	1.0	9.0		C_L = 50 pF	
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{PD}	Power Dissipation Capacitance			17				pF	(Note 7)	

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance, which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate)

Physical Dimensions inches (millimeters) unless otherwise noted

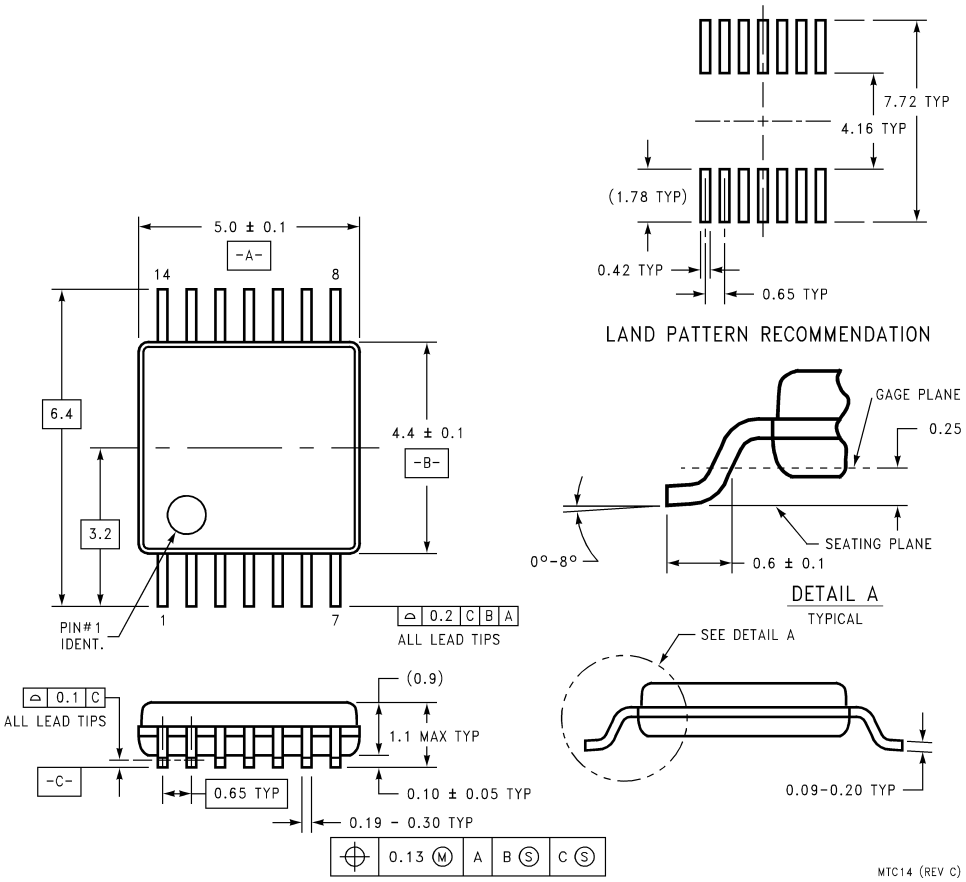


14-Lead Small Outline Integrated Circuit—JEDEC (M)
Package Number M14A



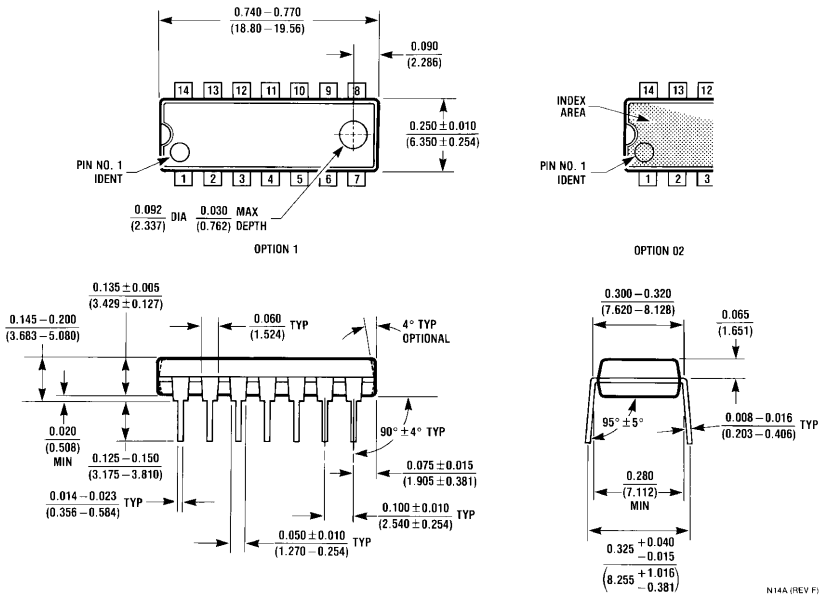
14-Lead Plastic EIAJ SOIC (SJ)
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic JEDEC TSSOP Type 1 (MTC)
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded DIP (P)
Package Number N14A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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July 1997
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74VHCT00A
Quad 2-Input NAND Gate

General Description

The VHCT00A is an advanced high-speed CMOS 2-Input NAND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

Features

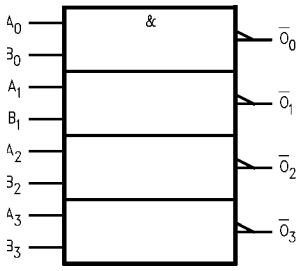
- High speed: t_{PD} = 5.0 ns (typ) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low noise: V_{OLP} = 0.8V (max)
- Low power dissipation:
  I_{CC} = 2 μA (max) at T_A = 25°C
- Pin and function compatible with 74HCT00

Ordering Code:

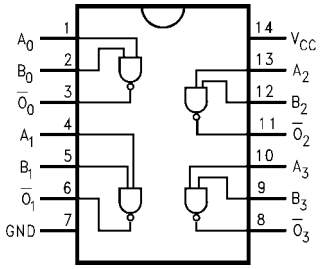
Order Number	Package Number	Package Description
74VHCT00AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHCT00ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT00AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT00AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	B	$\overline{O}$
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 2)	−0.5V to V_{CC} + 0.5V
(Note 3)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 4)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 5)

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 2)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{CC} = 0V.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active)

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
		4.5	3.94			3.80		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
		4.5			0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/ Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 6)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 6)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 6)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 6)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

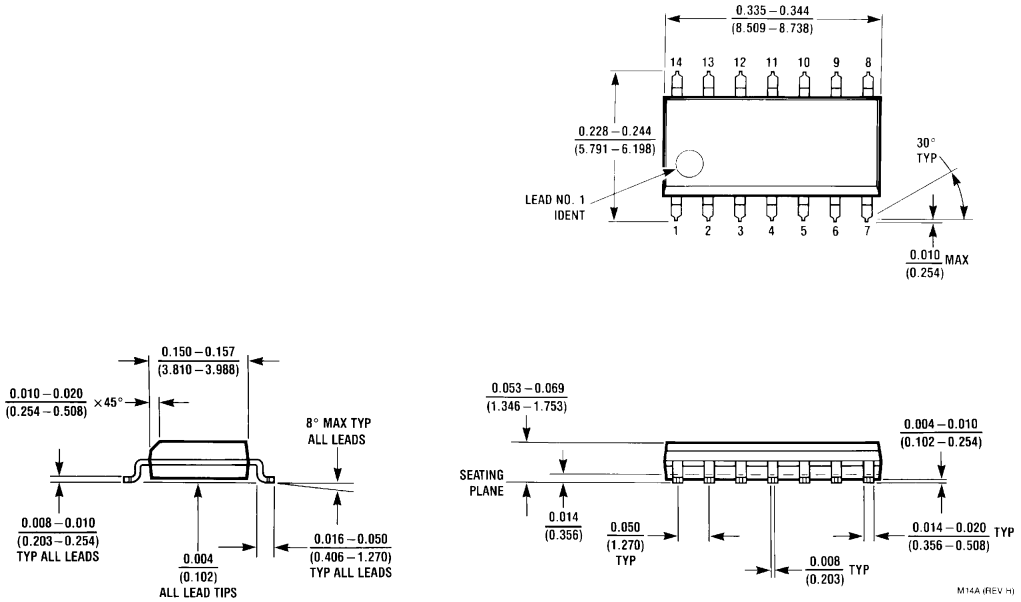
Note 6: Parameter guaranteed by design.

AC Electrical Characteristics

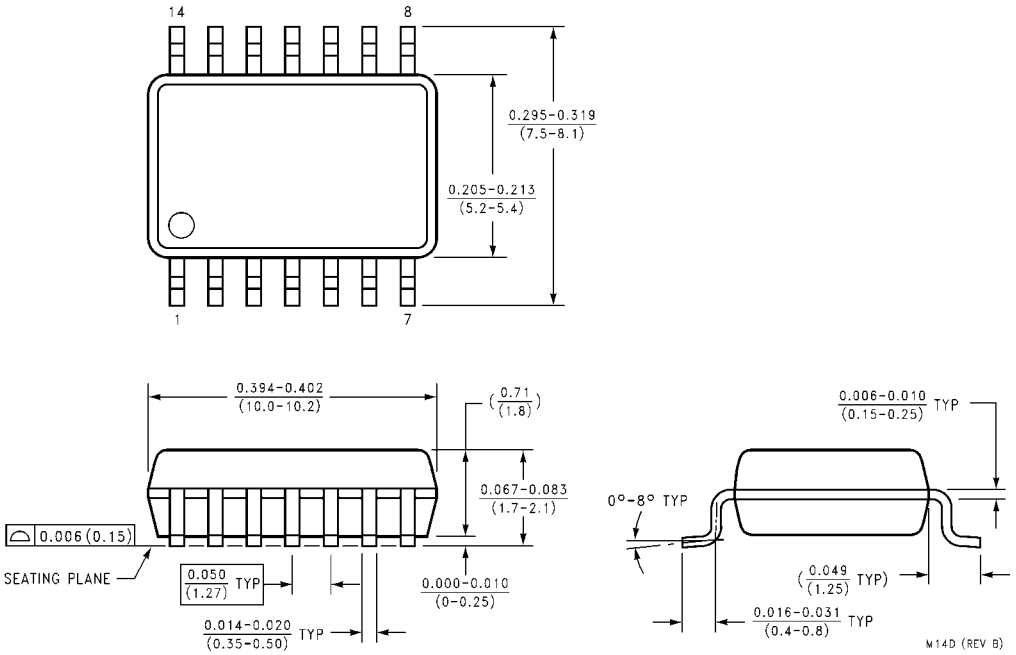
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	5.0 ± 0.5		5.0	6.9	1.0	8.0	ns	C_L = 15 pF
t_{PHL}				5.5	7.9	1.0	9.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			17				pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance, which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate)

Physical Dimensions inches (millimeters) unless otherwise noted

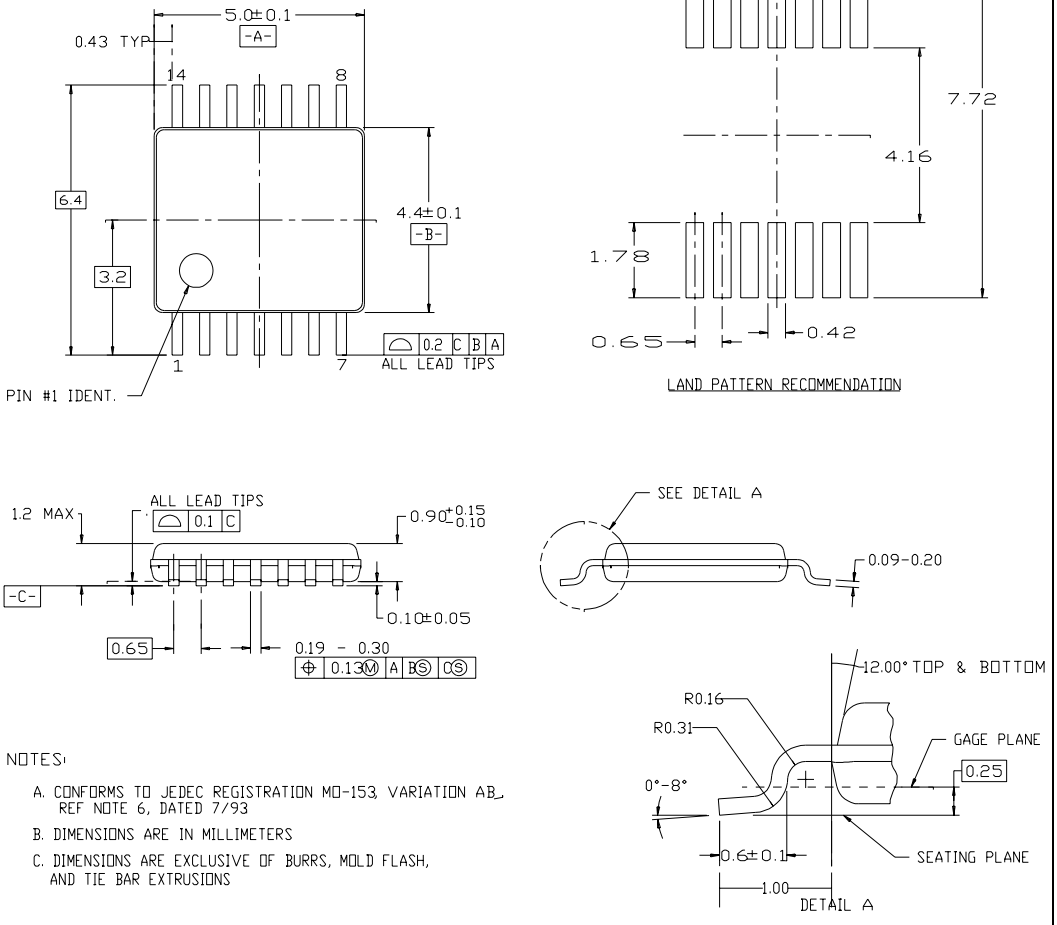


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

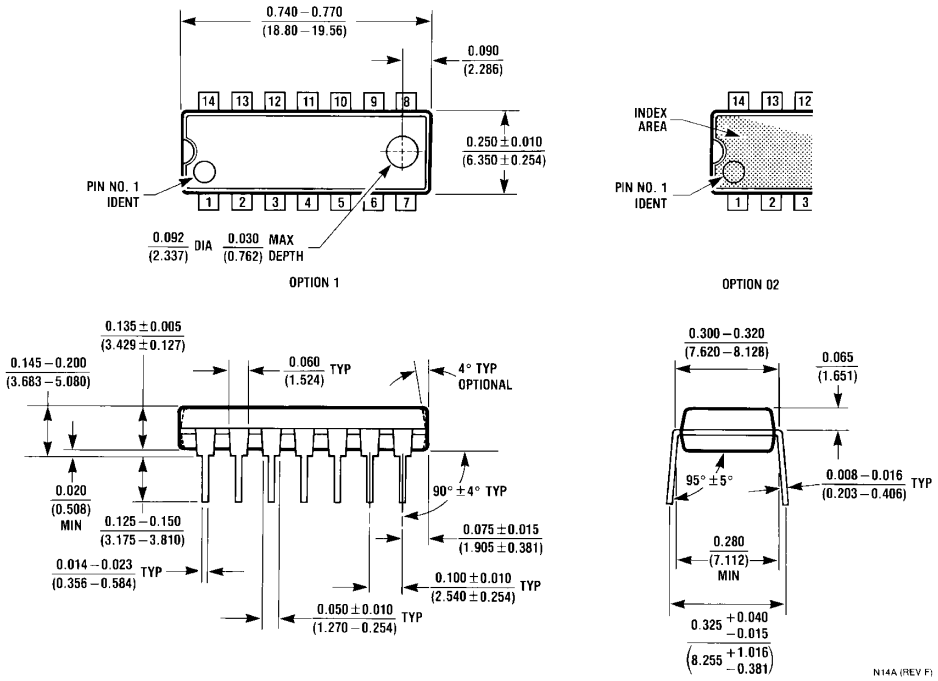
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

December 1997

74VHC04 • 74VHCT04
Hex Inverter

General Description

The VHC/VHCT04 is an advanced high speed CMOS INVERTER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0V–7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC t_{pd} = 3.8 ns (typ) at V_{CC} = 5V
  VHCT t_{pd} = 4.7 ns (typ) at V_{CC} = 5V
- High noise immunity:
  VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection:
  VHC inputs only
  VHCT inputs and outputs
- Low Noise:
  VHC V_{OLP} = 0.4V (typ
  VHCT V_{OLP} = 0.8V (typ)
- Low power dissipation:
  I_{CC} = 2 µA (Max) @ T_A = 25˚C
- Pin and function compatible with 74HC/HCT04

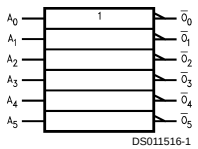
Ordering Code:

Commercial	Package Number	Package Description
74VHC04M	M14A	14-Lead Molded JEDEC SOIC
74VHC04SJ	M14D	14-Lead Molded EIAJ SOIC
74VHC04MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHC04N	N14A	14-Lead Molded DIP
74VHCT04M	M14A	14-Lead Molded JEDEC SOIC
74VHCT04SJ	M14D	14-Lead Molded EIAJ SOIC
74VHCT04MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHCT04N	N14A	14-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



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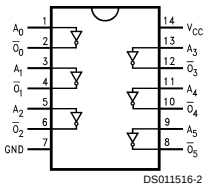
Connection Diagram

Pin Assignment for DIP, TSSOP, and SOIC



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Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	O
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 2)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions

(Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to +5.5V
VHCT	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	
74VHC/VHCT	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: $V_{OUT} > V_{CC}$ only if output is in H state.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = +50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
			2.5			2.4		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
					0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V	
									Other Inputs = V_{CC} or GND	
I_{OPD}	Output Leakage Current	0.0			+0.5		+5.0	μA	V_{OUT} = 5.5V	
	(Power Down State)									

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 5)	Quiet Output MaximumDynamic V_{OL}	5.0	0.8	1.0	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	1.0	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$			$T_A = -40^\circ C$ to $+85^\circ C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL},	Propagation Delay	3.3 ±0.3		5.0	7.1	1.0	8.5	ns	C_L = 15 pF
t_{PLH}				7.5	10.6	1.0	12.0		C_L = 50 pF
		5.0 ±0.5		3.8	5.5	1.0	6.5	ns	C_L = 15 pF
				5.3	7.5	1.0	8.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 6)

Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/6 (per gate).

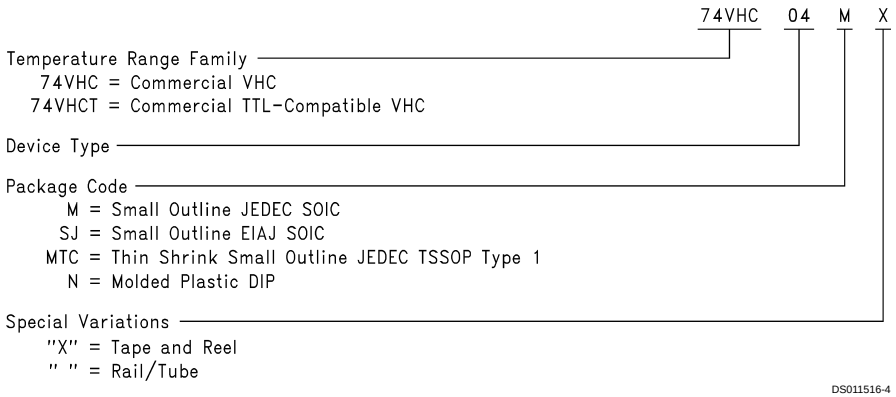
AC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$			$T_A = -40^\circ C$ to $+85^\circ C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL},	Propagation Delay	5.0 ±0.5		4.7	6.7	1.0	7.5	ns	C_L = 15 pF
t_{PLH}				5.5	7.7	1.0	8.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance			14				pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/6 (per gate).

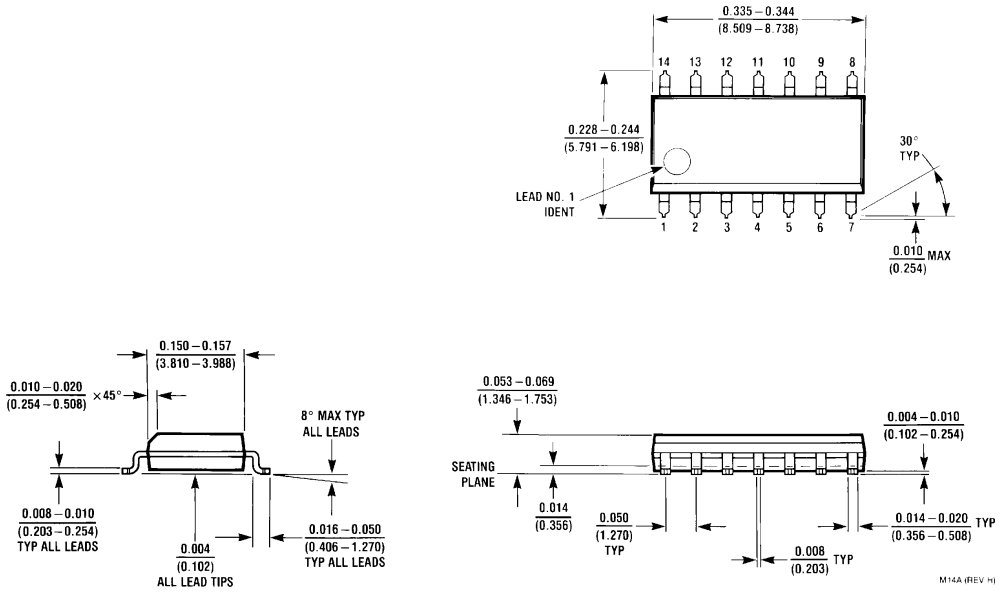
Ordering Information

The device number is used to form part of a simplified purchasing code, where the package type and temperature range are defined as follows:



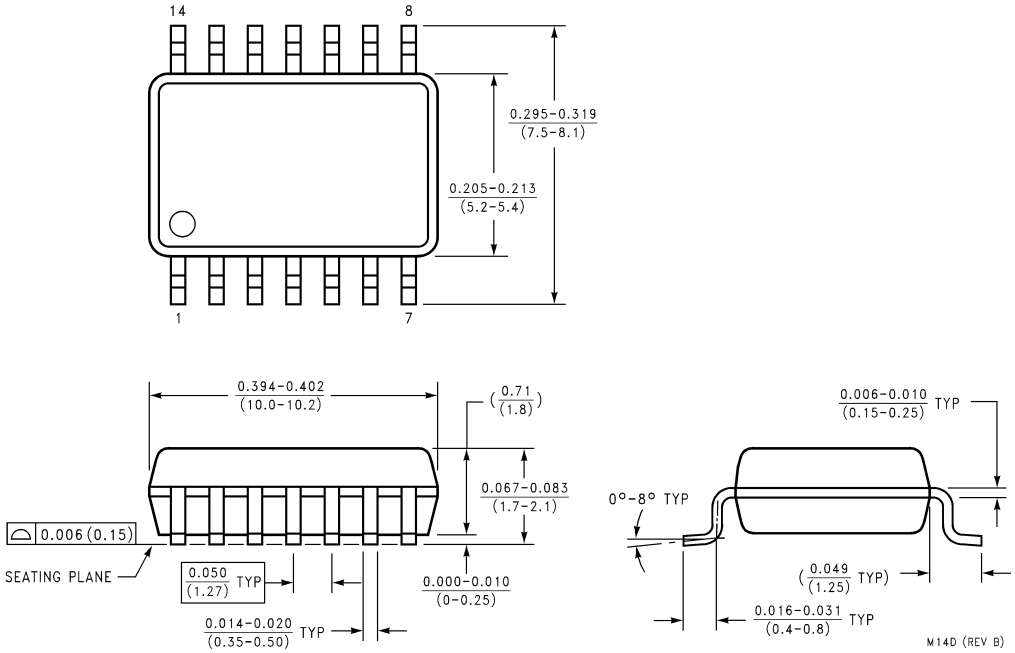
DS011516-4

Physical Dimensions inches (millimeters) unless otherwise noted



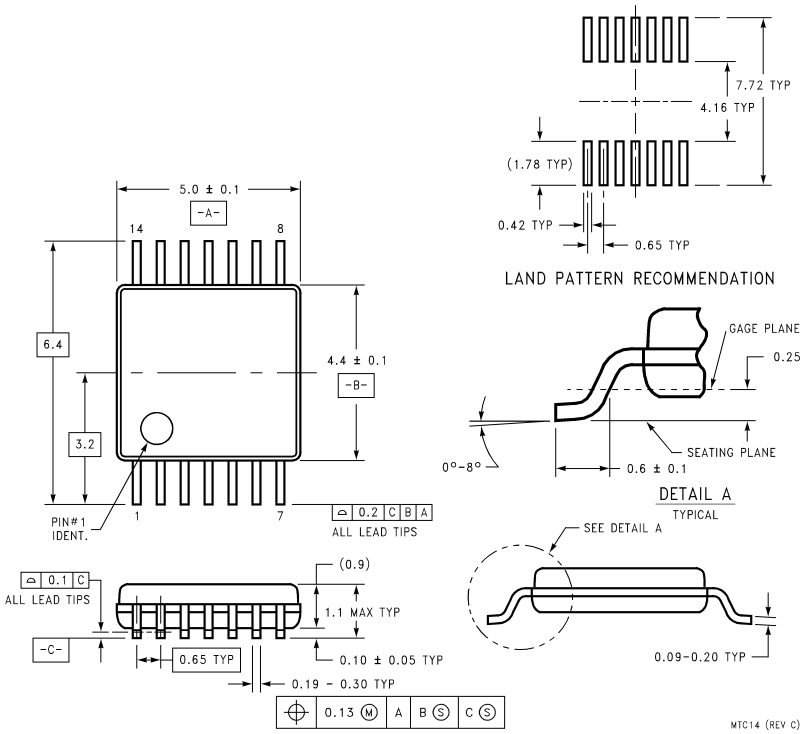
14-Lead Small Outline Integrated Circuit JEDEC SOIC (M)
Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



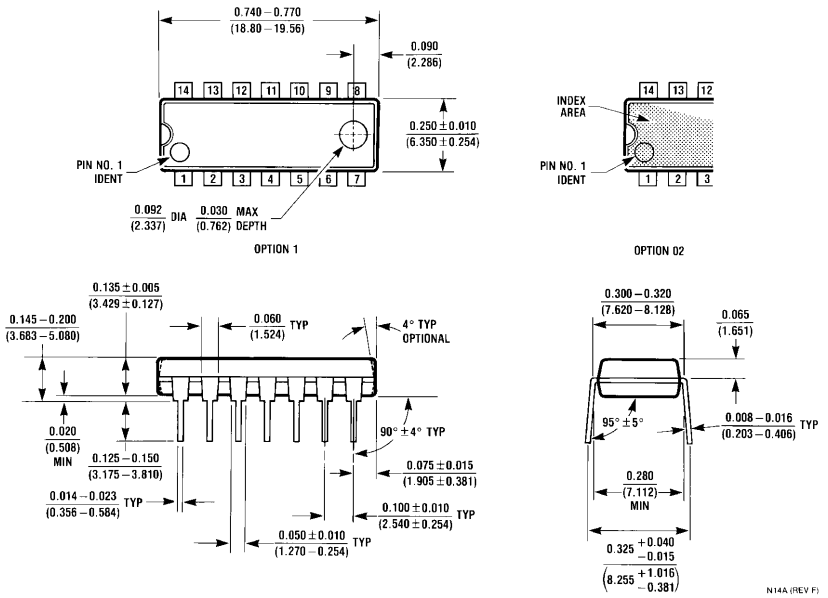
14-Lead Small Outline Package—EIAJ SOIC (SJ)
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded DIP
Package Number N14A

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FAIRCHILD SEMICONDUCTOR™

June 1997
Revised March 1999

74VHCT04A
Hex Inverter

General Description

The VHCT04A is an advanced high speed CMOS Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

Features

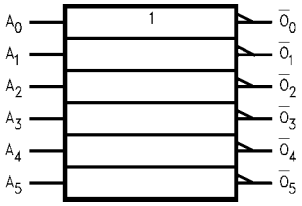
- High speed: t_{PD} = 4.7 ns (typ) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low noise: V_{OLP} = 1.0V (max)
- Low power dissipation:
  I_{CC} = 2 µA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT04

Ordering Code:

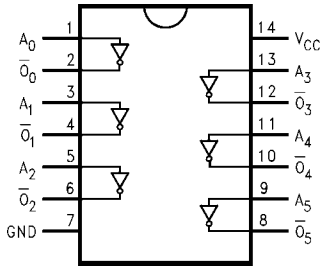
Order Number	Package Number	Package Description
74VHCT04AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHCT04ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT04AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT04AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	$\overline{O}$
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 2)	−0.5V to V_{CC} + 0.5V
(Note 3)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 4)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 5)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 2)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{CC} = 0V.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active)

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IL}	I_{OH} = −50 μA
			3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
					0.36		0.44	V		I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 6)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.8	1.0	V	C_L = 50 pF
V_{OLV} (Note 6)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	1.0	V	C_L = 50 pF
V_{IHD} (Note 6)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 6)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

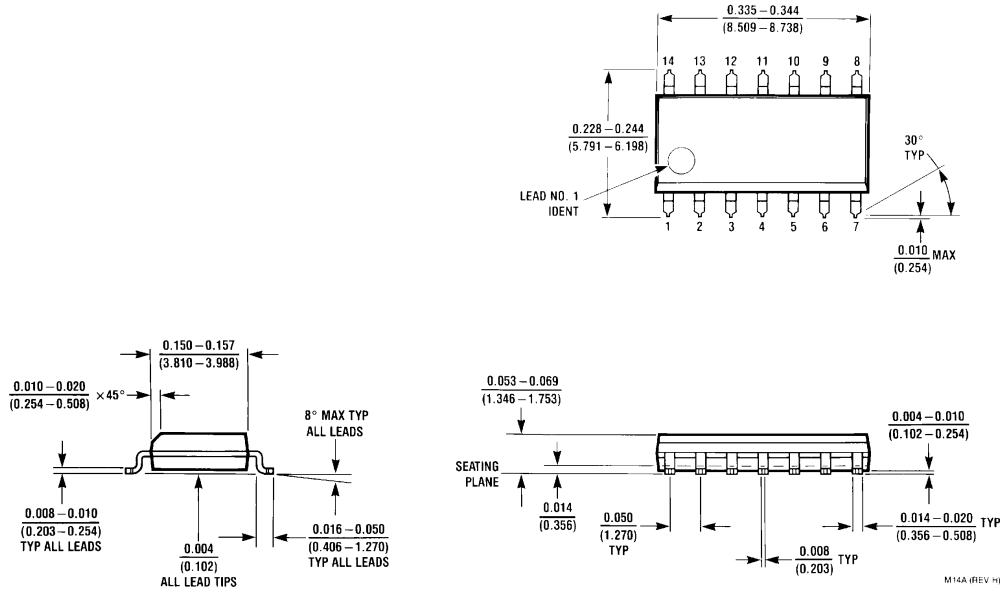
Note 6: Parameter guaranteed by design.

AC Electrical Characteristics

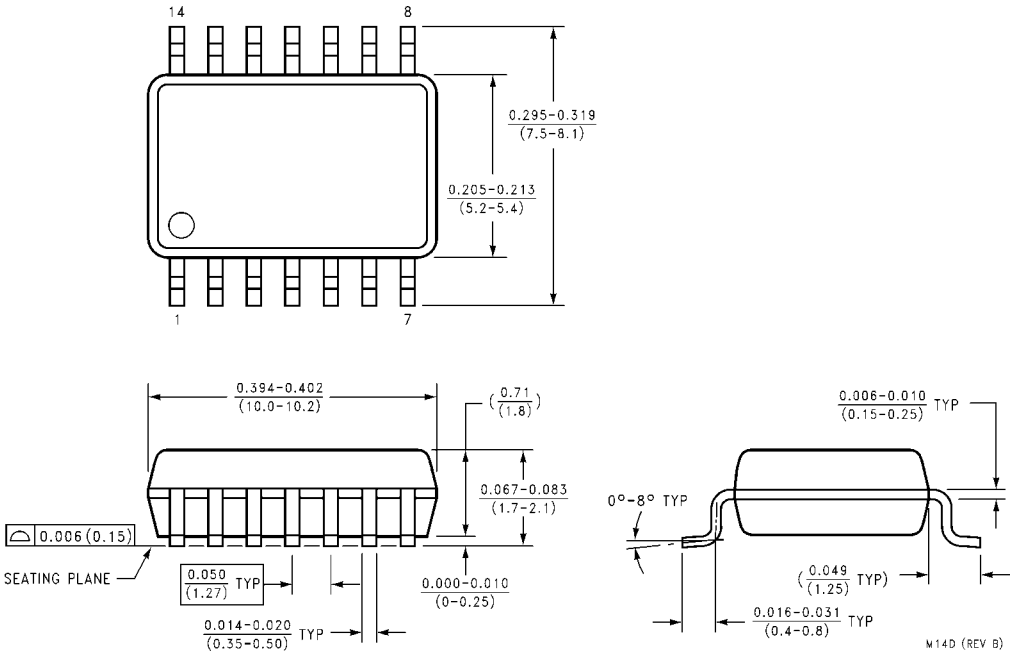
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL}	Propagation Delay	5.0 ± 0.5		4.7	6.7	1.0	7.5	ns	C_L = 15 pF
t_{PLH}				5.5	7.7	1.0	8.5		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance			11				pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/6 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

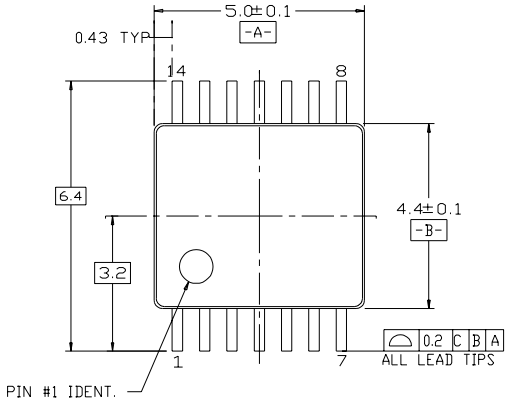


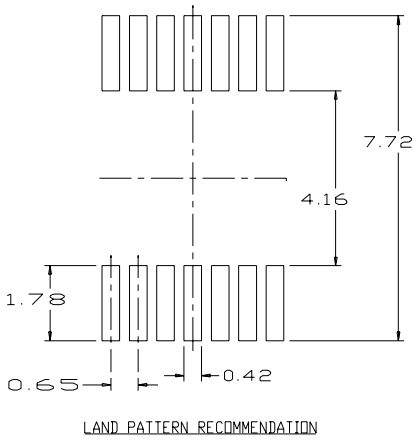
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

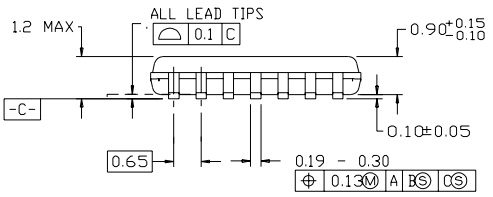


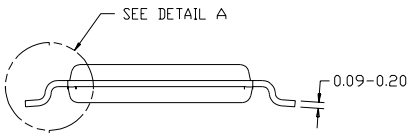
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

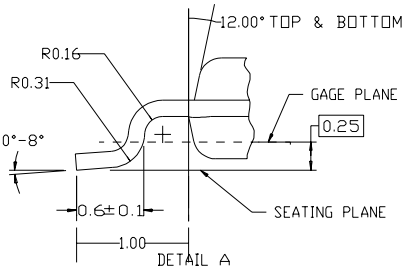
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)











NOTES:

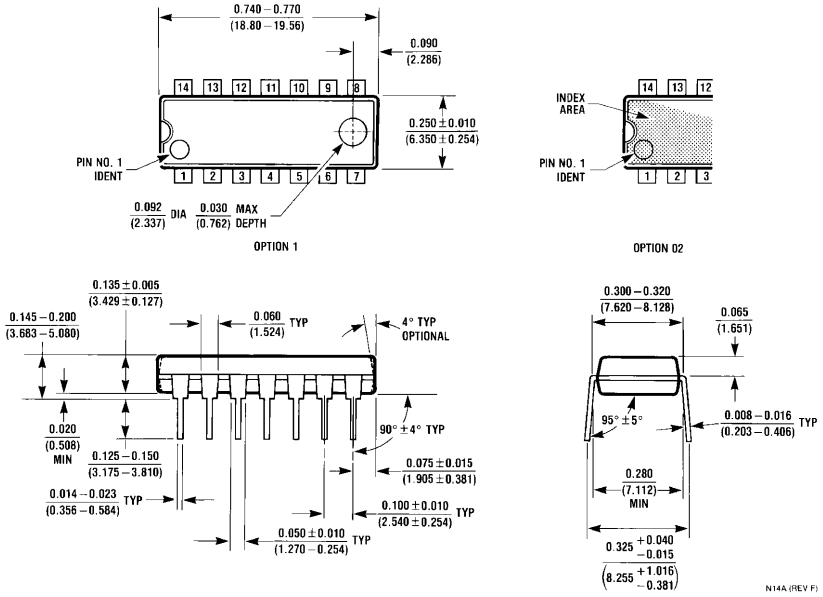
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

January 1998

74VHC08 • 74VHCT08
Quad 2-Input AND Gate

General Description

The VHC/VHCT08 is an advanced high speed CMOS 2 Input AND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- Low power dissipation:
  I_{CC} = 2 µA (Max) @ T_A = 25˚C
- High Speed:
  t_{pd} = 4.3 ns (typ) at T_A = 25˚C
- High noise immunity:
  VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection:
  VHC inputs only
  VHCT inputs and outputs
- Low noise:
  V_{OLP} = 0.8V (max)
- Pin and function compatible with 74HC/HCT08

Note: Add external pull up resistor to VHCT outputs to drive CMOS inputs.

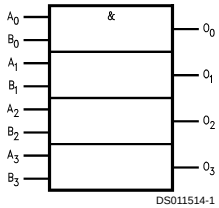
Ordering Code:

Commercial	Package Number	Package Description
74VHC08M	M14A	14-Lead Molded JEDEC SOIC
74VHC08SJ	M14D	14-Lead Molded EIAJ SOIC
74VHC08MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHC08N	N14A	14-Lead Molded DIP
74VHCT08M	M14A	14-Lead Molded JEDEC SOIC
74VHCT08SJ	M14D	14-Lead Molded EIAJ SOIC
74VHCT08MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHCT08N	N14A	14-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

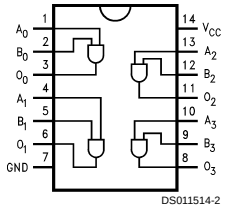
IEEE/IEC



DS011514-1

Connection Diagram

Pin Assignment for DIP, TSSOP, and SOIC



DS011514-2

Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Truth Table

A	B	O
L	L	L
L	H	L
H	L	L
H	H	H

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 2)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to +5.5V
VHCT	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: $V_{OUT} > V_{CC}$ only if output is in H state.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IH}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9		V	or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IH}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1	V	or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.3	0.8	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.3	−0.8	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
		4.5	2.5			2.4		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
		4.5			0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/ Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 5)	Quiet Output Maximum Dynamic V_{OL}		0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}		−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage			2.0	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage			0.8	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL}, t_{PLH}	Propagation Delay	3.3±0.3		6.2	8.8	1.0	10.5	ns	C_L = 15 pF
				8.7	12.3	1.0	14.0		C_L = 50 pF
		5.0±0.5		4.3	5.9	1.0	7.0	ns	C_L = 15 pF
				5.8	7.9	1.0	9.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 6)

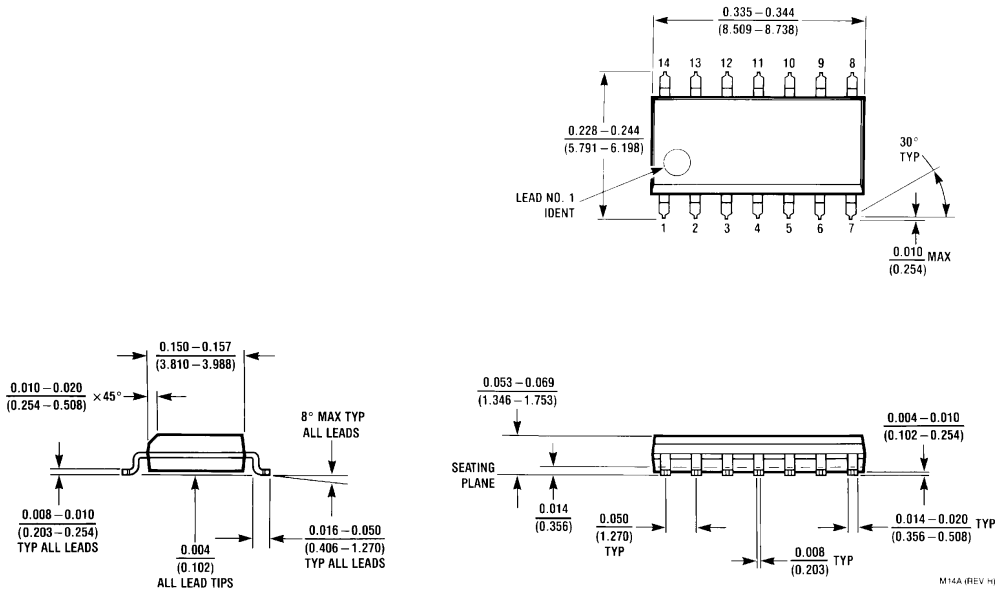
Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

AC Electrical Characteristics for VHCT

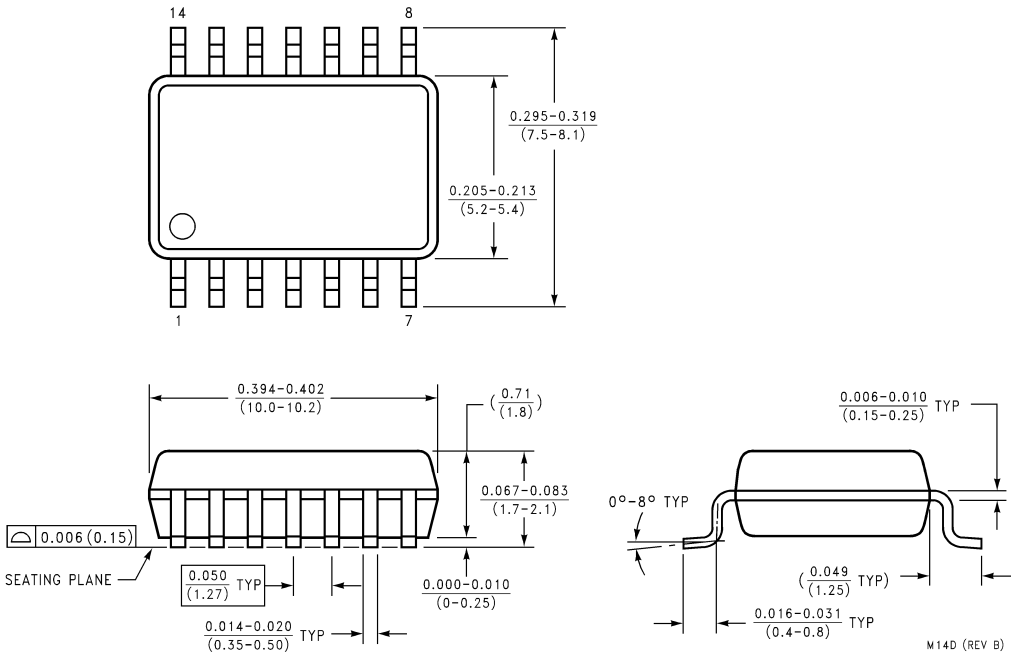
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH},	Propagation Delay	5.0		5.0	6.9	1.0	8.0	ns	C_L = 15 pF
t_{PHL}		±0.5		5.5	7.9	1.0	9.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance, which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate)

Physical Dimensions inches (millimeters) unless otherwise noted

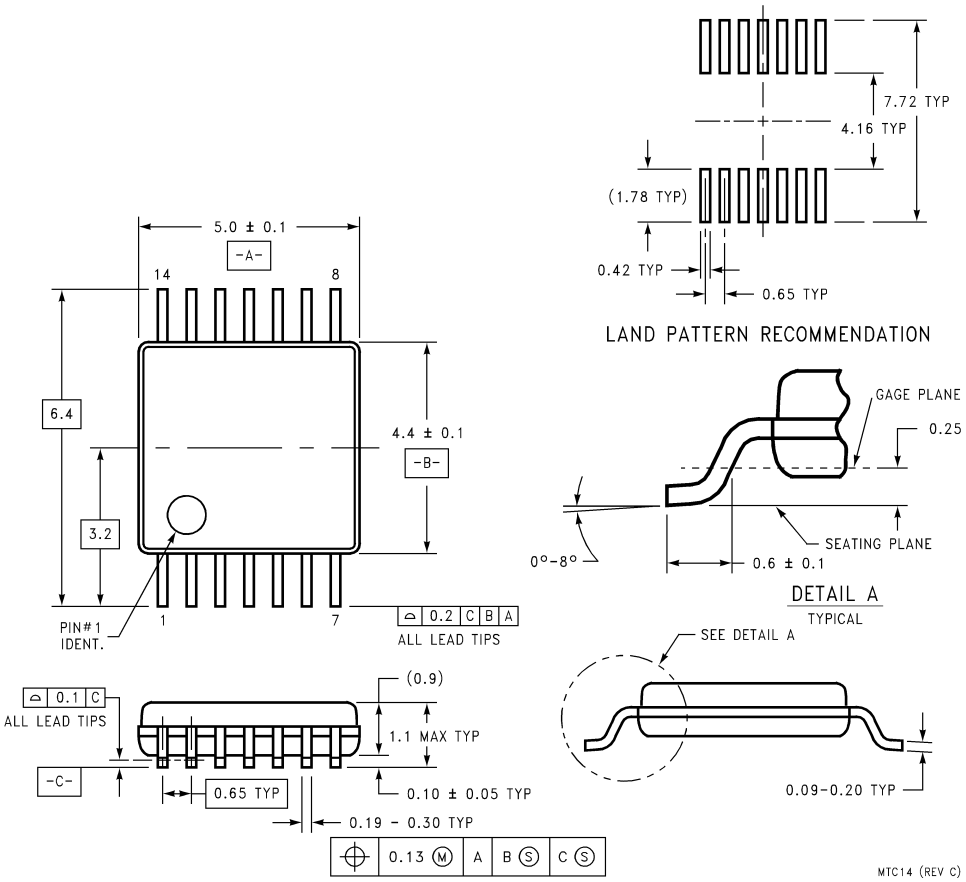


14-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Package Number M14A



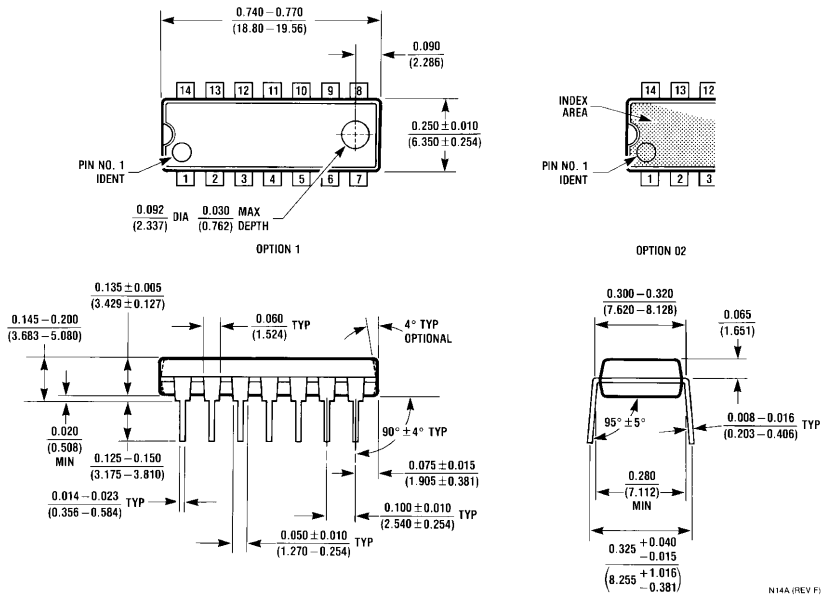
14-Lead Plastic EIAJ SOIC (SJ)
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded Dual-In-Line Package (MDIP)
Package Number N14A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1997
Revised March 1999

74VHCT08A
Quad 2-Input AND Gate

General Description

The VHCT08A is an advanced high speed CMOS 2 Input AND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

Features

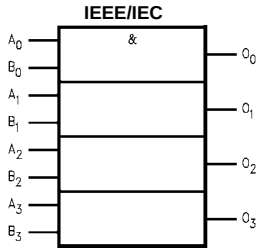
- High speed: t_{PD} = 5.0 ns (typ) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low noise: V_{OLP} = 0.8V (max)
- Low power dissipation:
  I_{CC} = 2 µA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT08

Ordering Code:

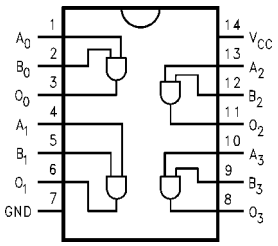
Order Number	Package Number	Package Description
74VHCT08AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHCT08ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT08AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT08AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

Truth Table

A	B	O
L	L	L
L	H	L
H	L	L
H	H	H

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 2)	−0.5V to V_{CC} + 0.5V
(Note 3)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK}) (Note 4)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 5)

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 2)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{CC} = 0V.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		4.5	3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		4.5			0.36		0.44	V		I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/ Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limit		
V_{OLP} (Note 6)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.4	0.8	V	C_L = 50 pF
V_{OLV} (Note 6)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.4	−0.8	V	C_L = 50 pF
V_{IHD} (Note 6)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 6)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

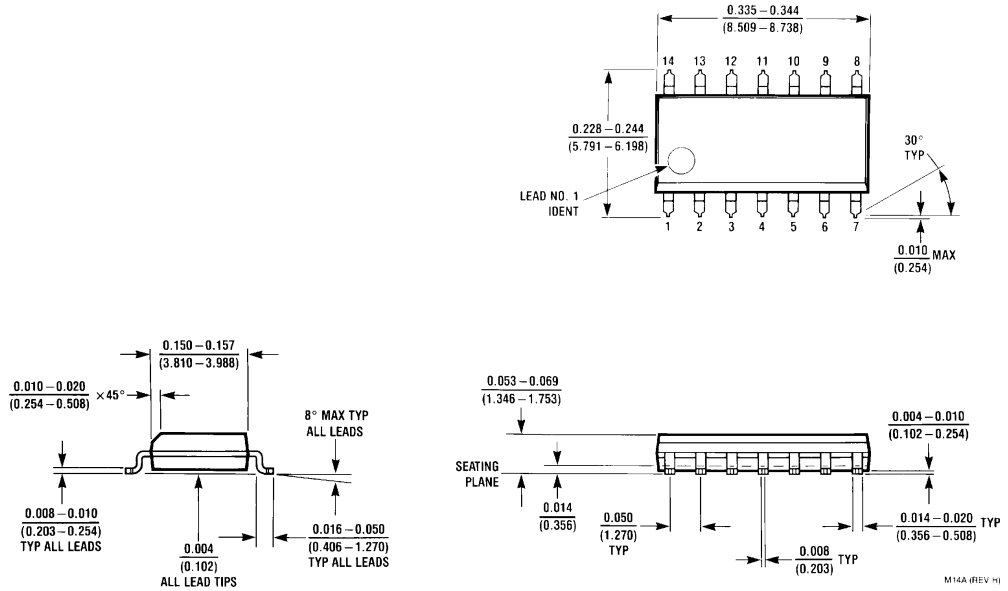
Note 6: Parameter guaranteed by design.

AC Electrical Characteristics

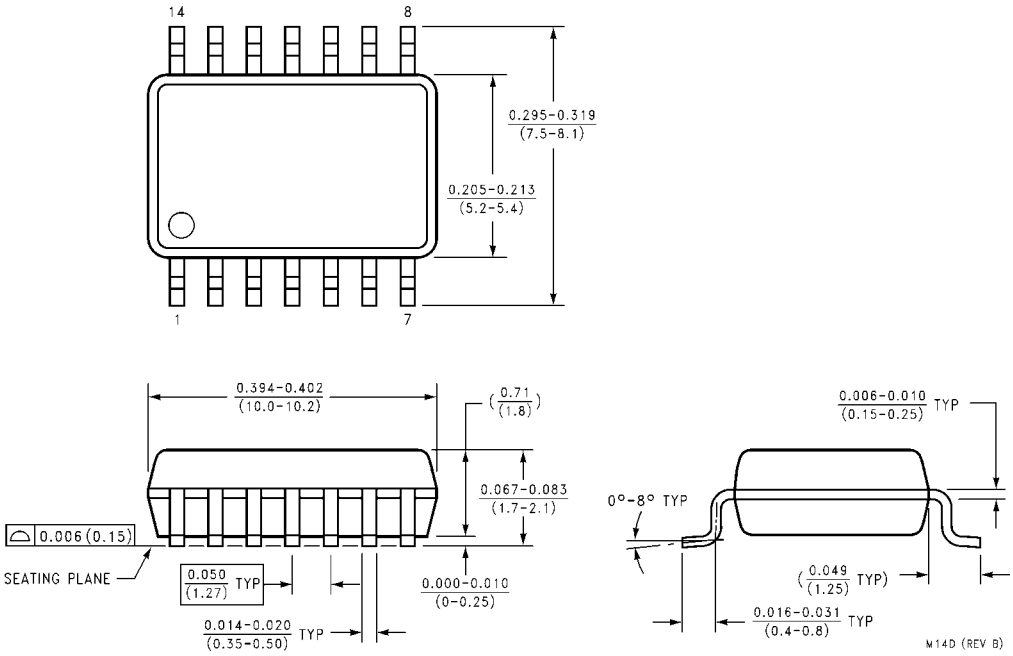
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	5.0		5.0	6.9	1.0	8.0	ns	$C_L = 15$ pF
t_{PHL}		±0.5		5.5	7.9	1.0	9.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance, which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/4$ (per gate)

Physical Dimensions inches (millimeters) unless otherwise noted

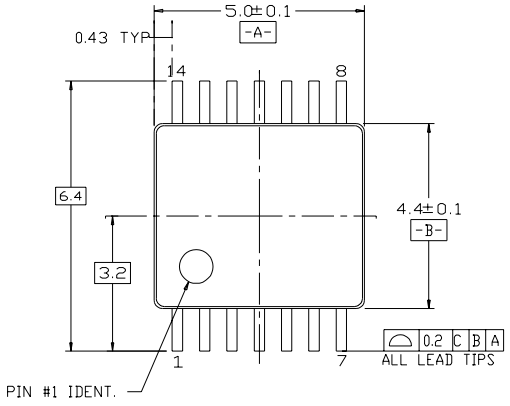


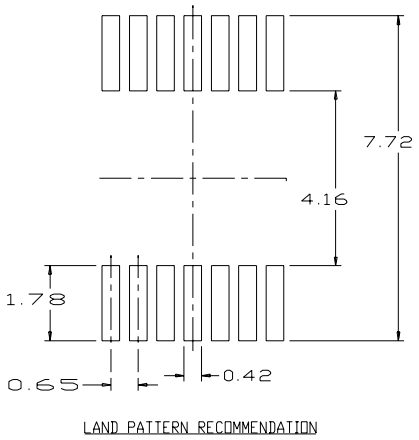
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

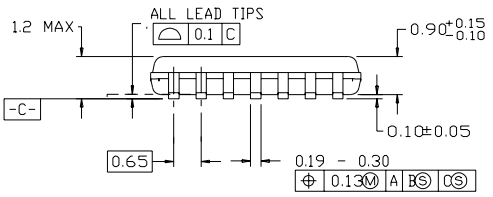


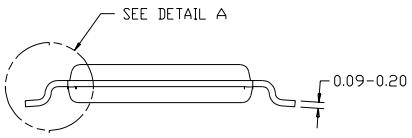
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

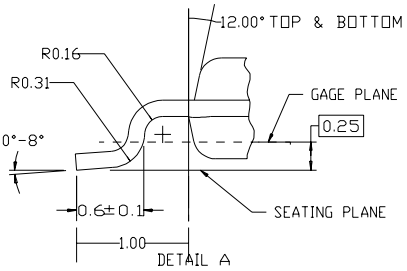
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)











NOTES:

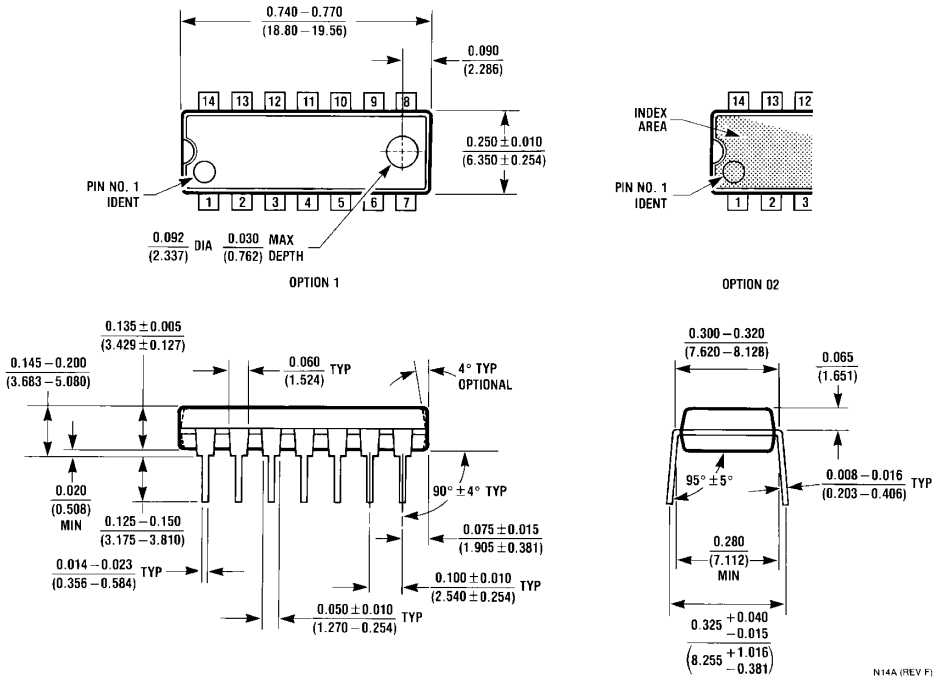
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

June 1997
Revised April 1999

74VHCT138A
3-to-8 Decoder/Demultiplexer

General Description

The VHCT138A is an advanced high speed CMOS 3-to-8 DECODER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A_0, A_1 and A_2) determine which one of the outputs ($\overline{O}_0$–$\overline{O}_7$) will go LOW. When enable input E_3 is held LOW or either $\overline{E}_1$ or $\overline{E}_2$ is held HIGH, decoding function is inhibited and all outputs go HIGH. E_3, $\overline{E}_1$ and $\overline{E}_2$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems. Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

Features

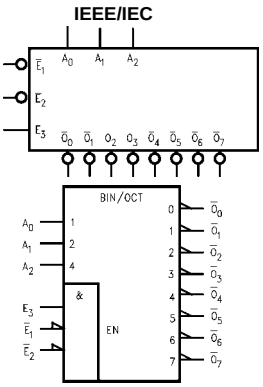
- High Speed: t_{PD} = 7.6 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max.) at T_A = 25°C
- Power down protection is provided on all inputs and outputs
- Pin and function compatible with 74HCT138

Ordering Code:

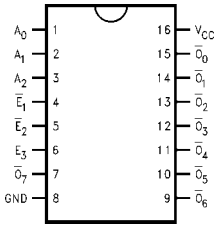
Order Number	Package Number	Package Description
74VHCT138AM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHCT138ASJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT138AMTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT138AN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Pin Descriptions

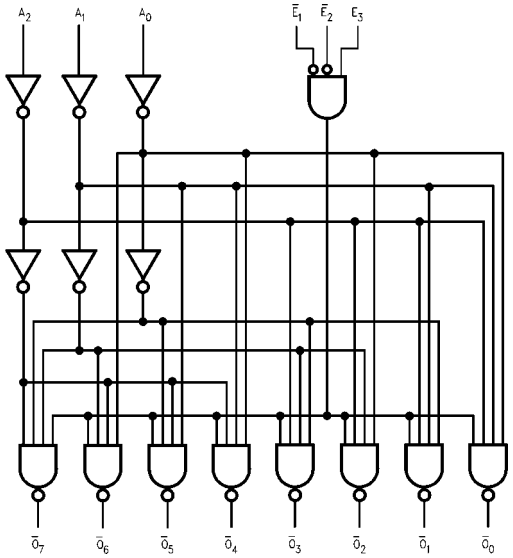
Pin Names	Description
A_0–A_2	Address Inputs
$\overline{E}_1$–$\overline{E}_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Table

Inputs						Outputs							
$\overline{E}_1$	$\overline{E}_2$	E_3	A_0	A_1	A_2	$\overline{O}_0$	$\overline{O}_1$	$\overline{O}_2$	$\overline{O}_3$	$\overline{O}_4$	$\overline{O}_5$	$\overline{O}_6$	$\overline{O}_7$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
L	L	H	H	L	L	H	L	H	H	H	H	H	H
L	L	H	L	H	L	H	H	L	H	H	H	H	H
L	L	H	H	H	L	H	H	H	L	H	H	H	H
L	L	H	L	L	H	H	H	H	H	L	H	H	H
L	L	H	H	L	H	H	H	H	H	H	L	H	H
L	L	H	L	H	H	H	H	H	H	H	H	L	H
L	L	H	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 2)	−0.5V to 7.0V
(Note 3)	−0.5V to V_{CC}+ 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 4)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 5)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 2)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: V_{CC} = 0V.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: V_{OUT} <GND, V_{OUT}> V_{CC} (Outputs Active).

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

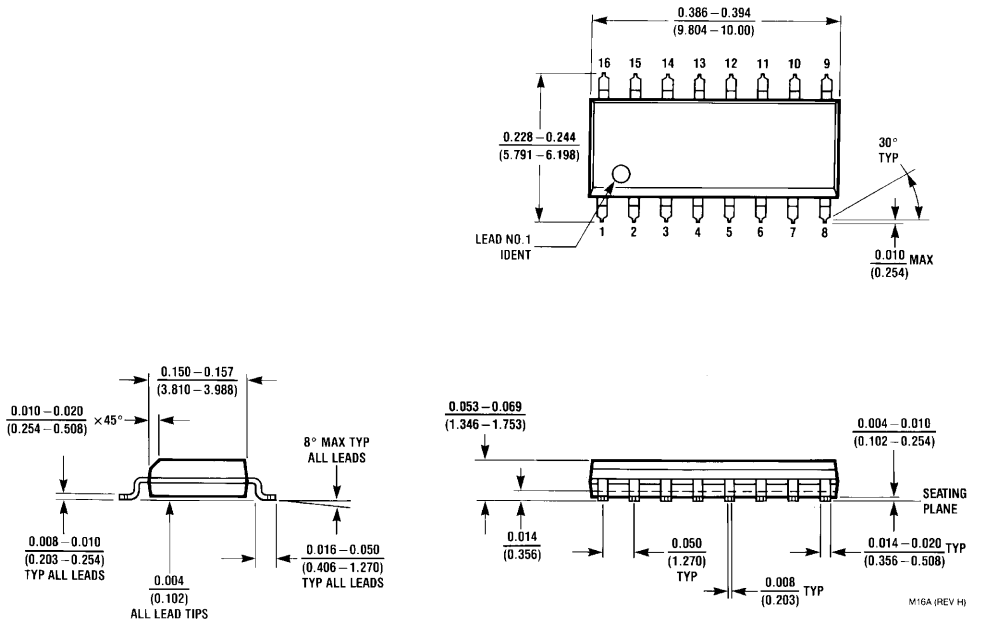
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5 – 5.5	2.0			2.0		V		
V_{IL}	LOW Level Input Voltage	4.5 – 5.5			0.8		0.8	V		
V_{OH}	HIGH Level	4.5	4.4	4.5		4.4		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
	Output Voltage	4.5	3.94			3.80			or V_{IL}	I_{OH} = −8 mA
V_{OL}	LOW Level	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
	Output Voltage	4.5			0.36		0.44		or V_{IL}	I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum $I_{CC/Input}$	5.5			1.35		1.50	mA	V_{in} = 3.4V other inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current	0			0.5		5.0	μA	V_{OUT} = 5.5V	

AC Electrical Characteristics

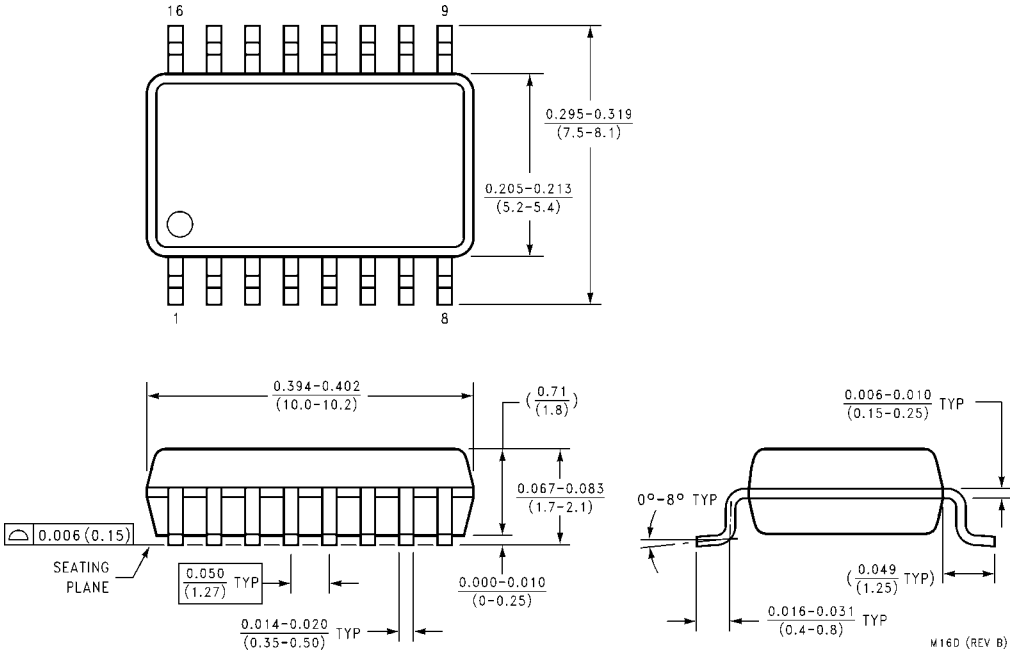
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay	5.0 ± 0.5		7.6	10.4	1.0	12.0	ns	C_L = 15 pF
t_{PHL}	A_n to $\overline{O}_n$			8.1	11.4	1.0	13.0		C_L = 50 pF
t_{PLH}	Propagation Delay	5.0 ± 0.5		6.6	9.1	1.0	10.5	ns	C_L = 15 pF
t_{PHL}	E_3 to $\overline{O}_n$			7.1	10.1	1.0	11.5		C_L = 50 pF
t_{PLH}	Propagation Delay	5.0 ± 0.5		7.0	9.6	1.0	11.0	ns	C_L = 15 pF
t_{PHL}	$\overline{E}_1$ or $\overline{E}_2$ to $\overline{O}_n$			7.5	10.6	1.0	12.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			49				pF	(Note 6)

Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}.

Physical Dimensions inches (millimeters) unless otherwise noted

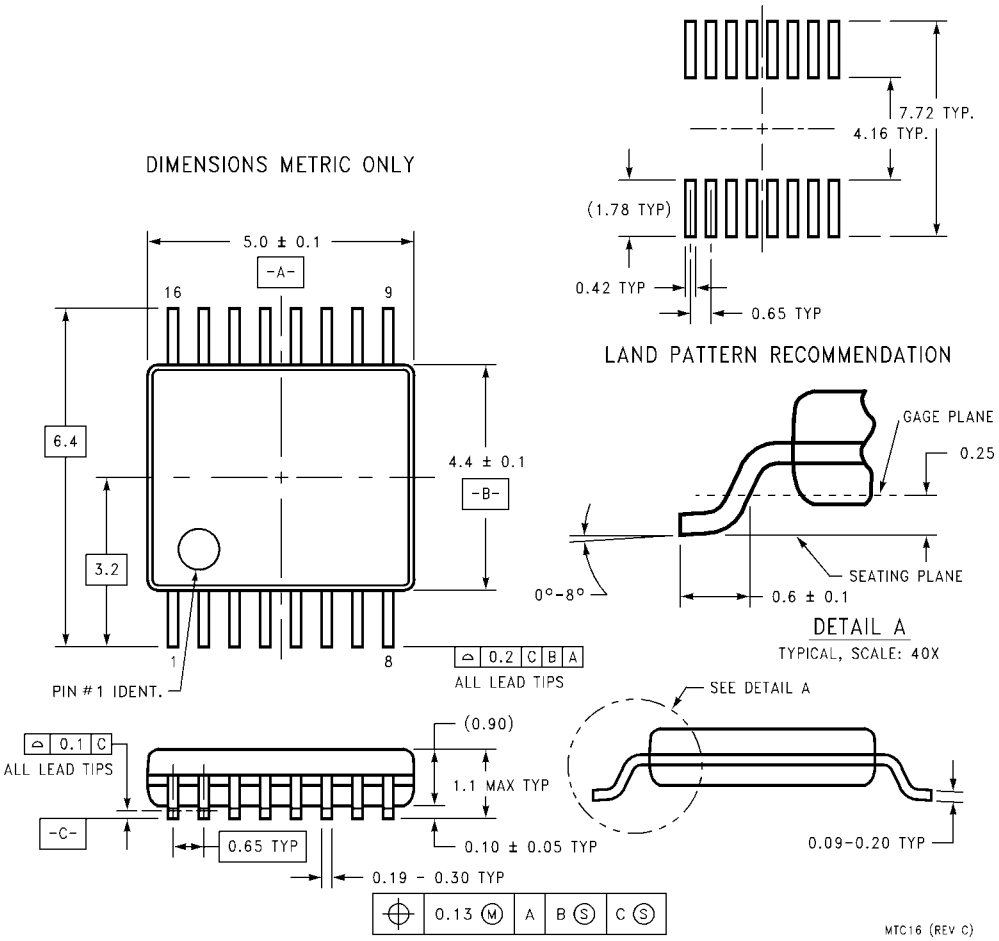


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
Package Number M16A



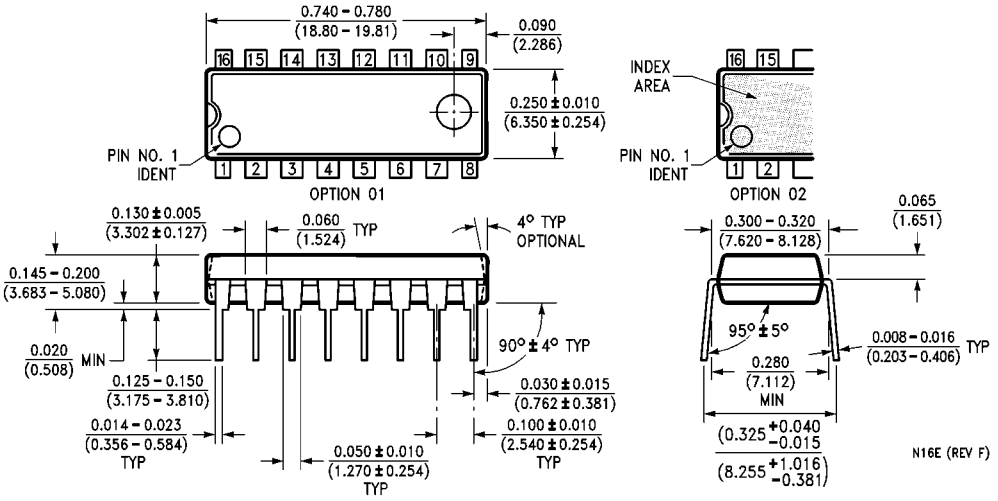
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N16E

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

December 1998
Revised March 1999

74VHCT14A
Hex Schmitt Inverter

General Description

The VHCT14A is an advanced high speed CMOS Hex Schmitt Inverter fabricated with silicon gate CMOS technology. The VHCT14A contains six independent inverters which are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

Features

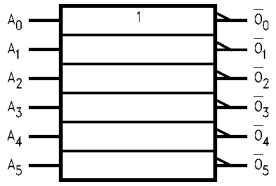
- High speed: t_{PD} = 5.0 ns (typ) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low noise: V_{OLP} = 1.0V (max)
- Low power dissipation:
  I_{CC} = 2 µA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT14

Ordering Code:

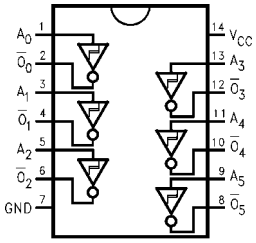
Order Number	Package Number	Package Description
74VHCT14AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VHCT14ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT14AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT14AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	$\overline{O}$
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 2)	−0.5V to V_{CC} + 0.5V
(Note 3)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK}) (Note 4)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 5)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 2)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{CC} = 0V.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active)

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_P	Positive Threshold Voltage	4.5			1.9		1.9	V		
		5.5			2.1		2.1			
V_N	Negative Threshold Voltage	4.5	0.5			0.5		V		
		5.5	0.6			0.6				
V_H	Hysteresis Voltage	4.5	0.4		1.4	0.4	1.4	V		
		5.5	0.4		1.5	0.4	1.5			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IL}	I_{OH} = −50 μA
			3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
					0.36		0.44	V		I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 6)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.8	1.0	V	C_L = 50 pF
V_{OLV} (Note 6)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	1.0	V	C_L = 50 pF
V_{IHD} (Note 6)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 6)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

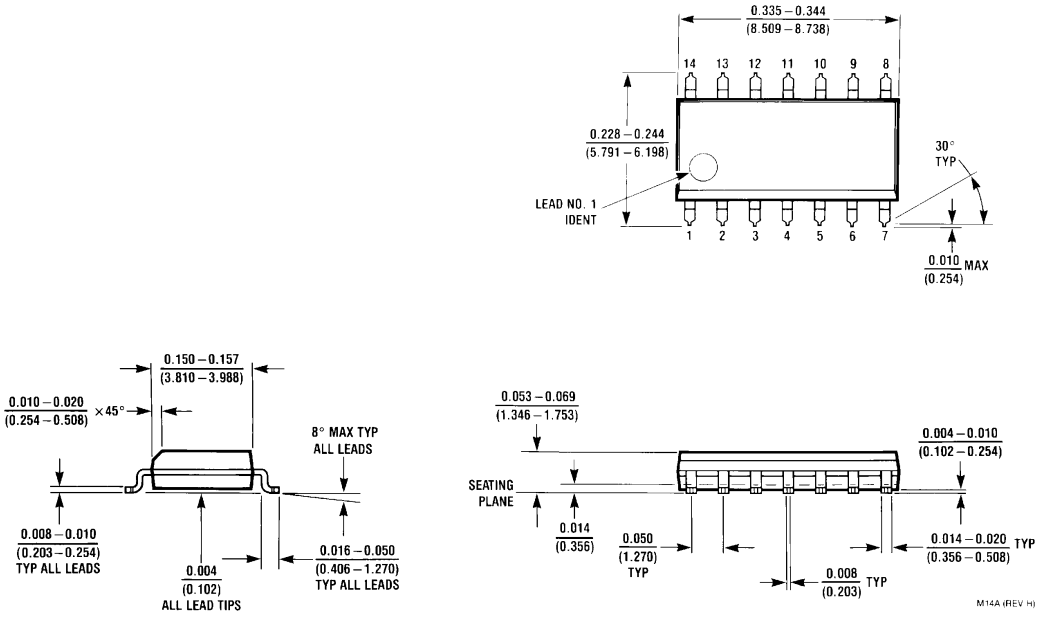
Note 6: Parameter guaranteed by design.

AC Electrical Characteristics

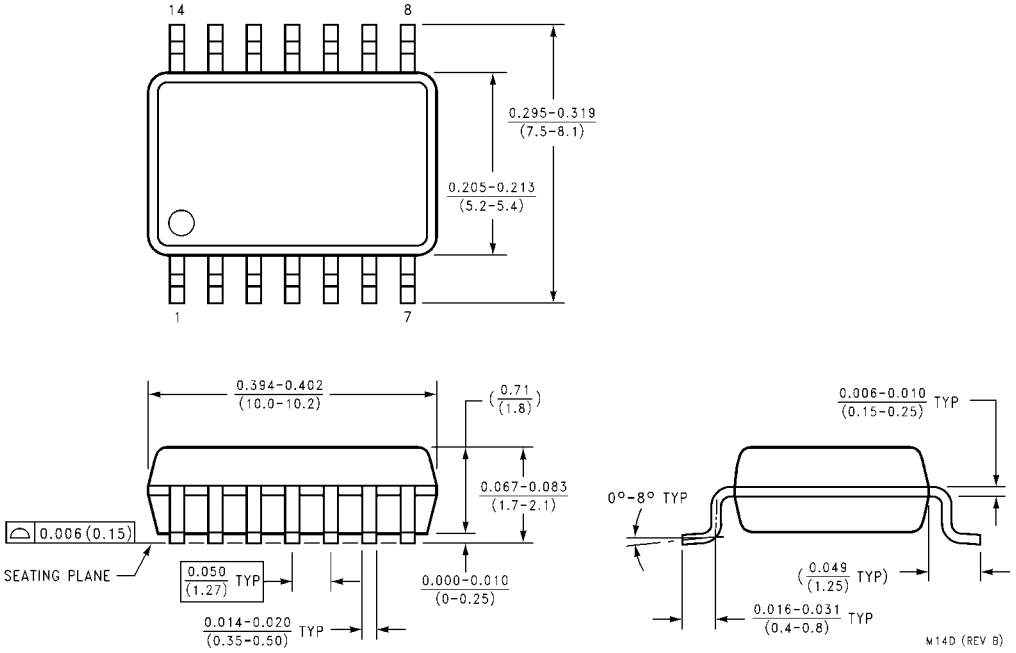
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL}	Propagation Delay	5.0 ± 0.5		5.0	7.6	1.0	9.0	ns	$C_L = 15$ pF
t_{PLH}				6.5	9.6	1.0	11.0	ns	$C_L = 50$ pF
C_{IN}	Input Capacitance			2	10		10	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance			11				pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/6 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

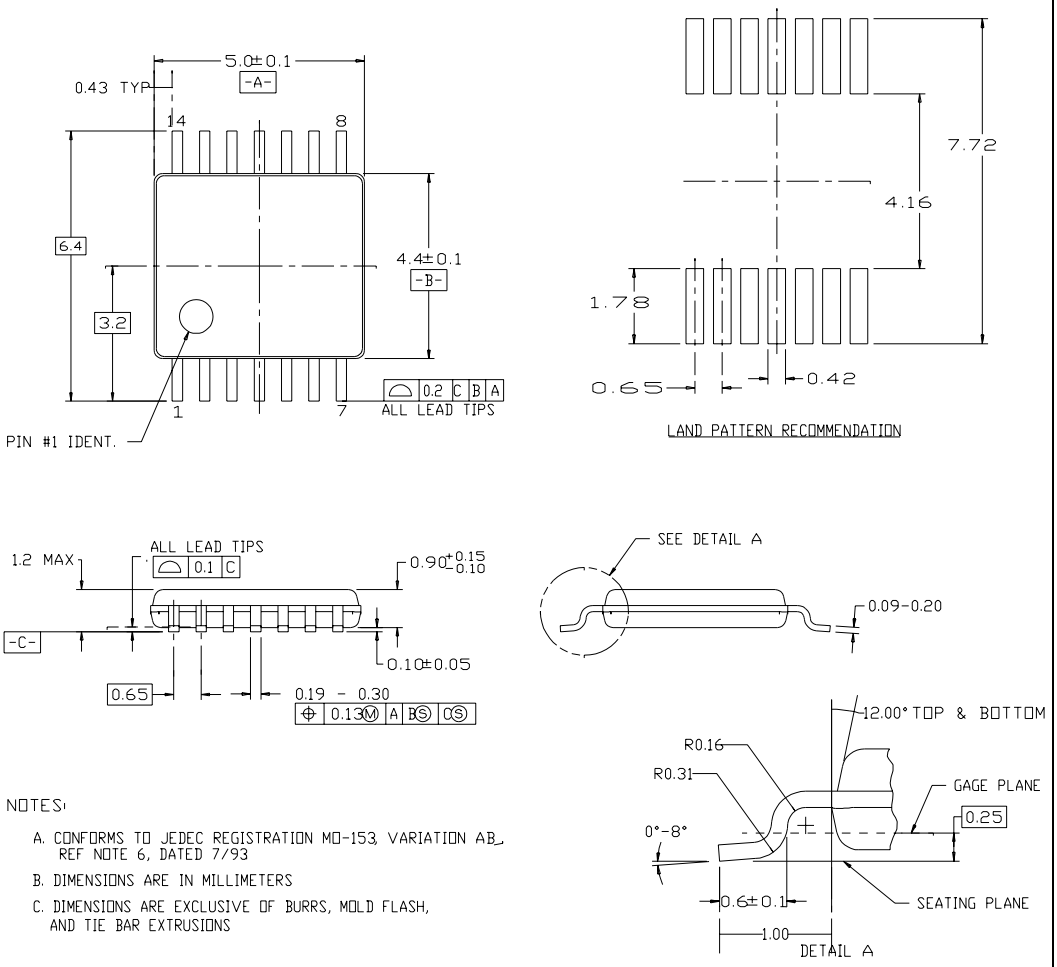


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

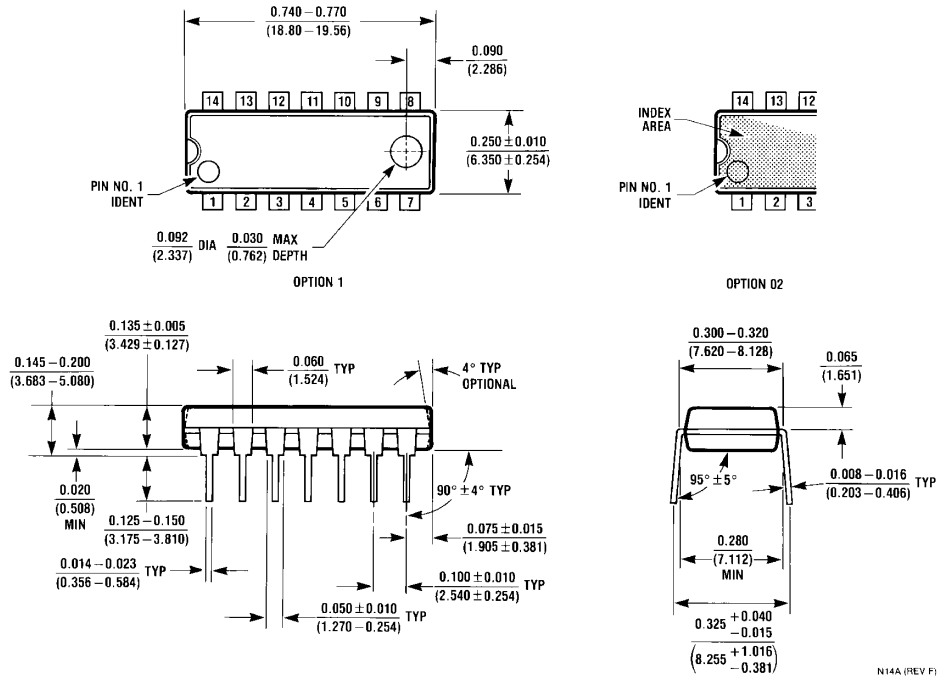
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

National Semiconductor

November 1995

74VHC240 • 74VHCT240
Octal Buffer/Line Driver with TRI-STATE® Outputs

General Description

The 'VHC240 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The 'VHC240 is an inverting TRI-STATE buffer having two active-low output enables. These devices are designed to drive buslines or buffer memory address registers.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High noise immunity: $V_{NIH} = V_{NIL} = 28\%\ V_{CC}$ (min)
- Power down protection: inputs only
- Low noise: $V_{OLP} = 0.9V$ (max)
- Low power dissipation: $I_{CC} = 4\ \mu A$ (max) @ $T_A = 25°C$
- Balanced propagation delays: $t_{PLH} \cong t_{PHL}$
- Pin and function compatible with 74HC/HCT240

THE 74VHCT240 IS ADVANCE INFORMATION ONLY

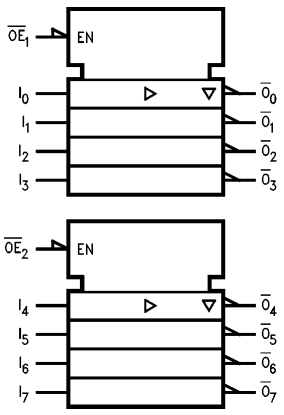
NOTE: ADD EXTERNAL PULL UP RESISTOR TO VHCT OUTPUTS TO DRIVE CMOS INPUTS

Commercial	Package Number	Package Description
74VHC240M	M20B	20-Lead Molded JEDEC SOIC
74VHC240SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC240MSC	MSC20	20-Lead Molded EIAJ Type 1 SSOP
74VHC240MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHC240N	N20A	20-Lead Molded DIP

Note: Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. EIAJ Type 1 SSOP available on tape and reel only, order MSCX.

Logic Symbol

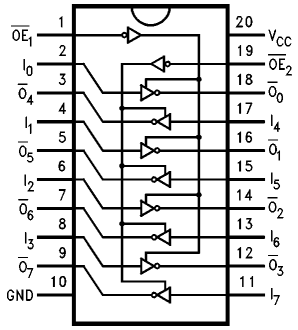
IEEE/IEC



TL/F/11506–1

Connection Diagram

Pin Assignment for DIP, SSOP, TSSOP and SOIC



TL/F/11506–2

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	TRI-STATE Output Enable Inputs
$I_0–I_7$	Inputs
$\overline{O}_0–\overline{O}_7$	Outputs TRI-STATE Outputs

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT*	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

*V_{OUT} > V_{CC} only if output is in H or Z state.

Note 1: *Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation outside databook specifications*.

Recommended Operating Conditions

Supply Voltage (V_{CC})	
VHC	2.0V to 5.5V
VHCT	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	
74VHC/VHCT	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC Only)	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ns/V ~ 20 ns/V

DC Characteristics for 'VHC Family Devices

Symbol	Parameter	V_{CC} (V)	74VHC T_A = 25°C			74VHC T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	TRI-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

DC Characteristics for 'VHC Family Devices

Symbol	Parameter	V_{CC} (V)	74VHC $T_A = 25°C$ Typ	74VHC $T_A = 25°C$ Limits	Units	Conditions
**V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	$C_L = 50$ pF
**V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	$C_L = 50$ pF
**V_{IHD}	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	$C_L = 50$ pF
**V_{ILD}	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	$C_L = 50$ pF

**Parameter guaranteed by design.

DC Characteristics for 'VHCT Family Devices (Preliminary)

Symbol	Parameter	V_{CC} (V)	74VHCT $T_A = 25°C$ Min	Typ	Max	54VHCT $T_A = -40°C$ to $+85°C$ Min	Max	Units	Conditions	
V_{IH}	High Level Input Voltage	4.5 5.5	2.0 2.0			2.0 2.0		V		
V_{IL}	Low Level Input Voltage	4.5 5.5			0.8 0.8		0.8 0.8	V		
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\ \mu A$
		4.5	2.5			2.4				$I_{OH} = -8$ mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50\ \mu A$
		4.5			0.36		0.44			$I_{OL} = 8$ mA
I_{OZ}	TRI-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	$V_{IN} = 5.5$V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	$V_{IN} = V_{CC}$ or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	$V_{IN} = 3.4$V, Other Inputs = V_{CC} or GND	
I_{OPD}	Output Leakage (Power Down State)	0.0			+0.5		+5.0	μA	$V_{OUT} = 5.5$V	

DC Characteristics for 'VHCT Family (Preliminary) :

Symbol	Parameter	V_{CC} (V)	74VHCT $T_A = 25°C$ Typ	74VHCT $T_A = 25°C$ Limits	Units	Conditions
V_{OLP}**	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	$C_L = 50$ pF
V_{OLV}**	Quiet Output Minimum Dynamic V_{OL}		−0.7	−1.0	V	$C_L = 50$ pF
V_{IHD}**	Minimum High Level Dynamic Input Voltage			2.0	V	$C_L = 50$ pF
V_{ILD}**	Maximum High Level Dynamic Input Voltage			0.8	V	$C_L = 50$ pF

**Parameter guaranteed by design.

AC Electrical Characteristics for 'VHC Family Devices

Symbol	Parameter	V_{CC} (V)	74VHC $T_A = 25°C$ Min	Typ	Max	74VHC $T_A = -40°C$ to $+85°C$ Min	Max	Units	Conditions	
t_{PLH} t_{PHL}	Propagation Delay Time	3.3 ±0.3		5.3	7.5	1.0	9.0	ns		$C_L = 15$ pF
				7.8	11.0	1.0	12.5			$C_L = 50$ pF
		5.0 ±0.5		3.6	5.5	1.0	6.5	ns		$C_L = 15$ pF
				5.1	7.5	1.0	8.5			$C_L = 50$ pF
t_{PZL} t_{PZH}	TRI-STATE Output Enable Time	3.3 ±0.3		6.6	10.6	1.0	12.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
				9.1	14.1	1.0	16.0			$C_L = 50$ pF
		5.0 ±0.5		4.7	7.3	1.0	8.5	ns		$C_L = 15$ pF
				6.2	9.3	1.0	10.5			$C_L = 50$ pF
t_{PLZ} t_{PHZ}	TRI-STATE Output Disable Time	3.3 ±0.3		10.3	14.0	1.0	16.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
		5.0 ±0.5		6.7	9.2	1.0	10.5			$C_L = 50$ pF
t_{OSLH} t_{OSHL}	Output to Output Skew	3.3 ±0.3			1.5		1.5	ns	(Note 1)	$C_L = 50$ pF
		5.0 ±0.5			1.0		1.0			$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			17				pF	(Note 2)	

Note 1: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

AC Electrical Characteristics for 'VHCT (Preliminary)

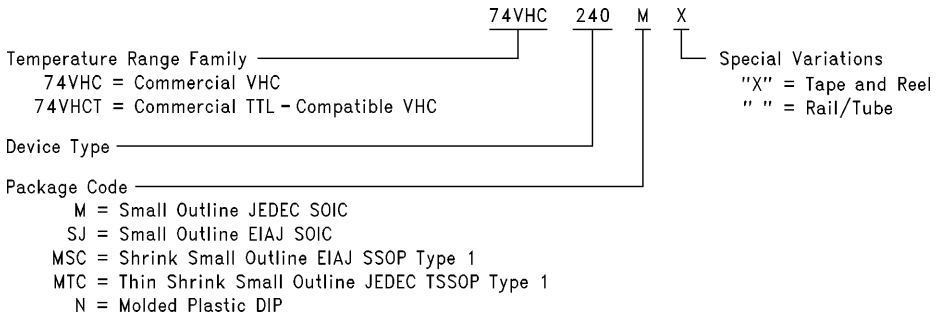
Symbol	Parameter	V_{CC} (V)	74VHCT $T_A = 25°C$			74VHCT $T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}, t_{PHL}	Propagation Delay Time	5.0 ±0.5		5.4	7.4	1.0	8.5	ns		$C_L = 15$ pF
				5.9	8.4	1.0	9.5			$C_L = 50$ pF
t_{PZL}, t_{PZH}	TRI-STATE Output Enable Time	5.0 ±0.5		7.7	10.4	1.0	12.0	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
				8.2	11.4	1.0	13.0			$C_L = 50$ pF
t_{PLZ}, t_{PHZ}	TRI-STATE Output Disable Time	5.0 ±0.5		8.8	11.4	1.0	13.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{OSLH}, t_{OSHL}	Output to Output Skew	5.0 ±0.5			1.0		1.0	ns	(Note 1)	$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	$V_{CC} = 5.0V$	
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 2)	

Note 1: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

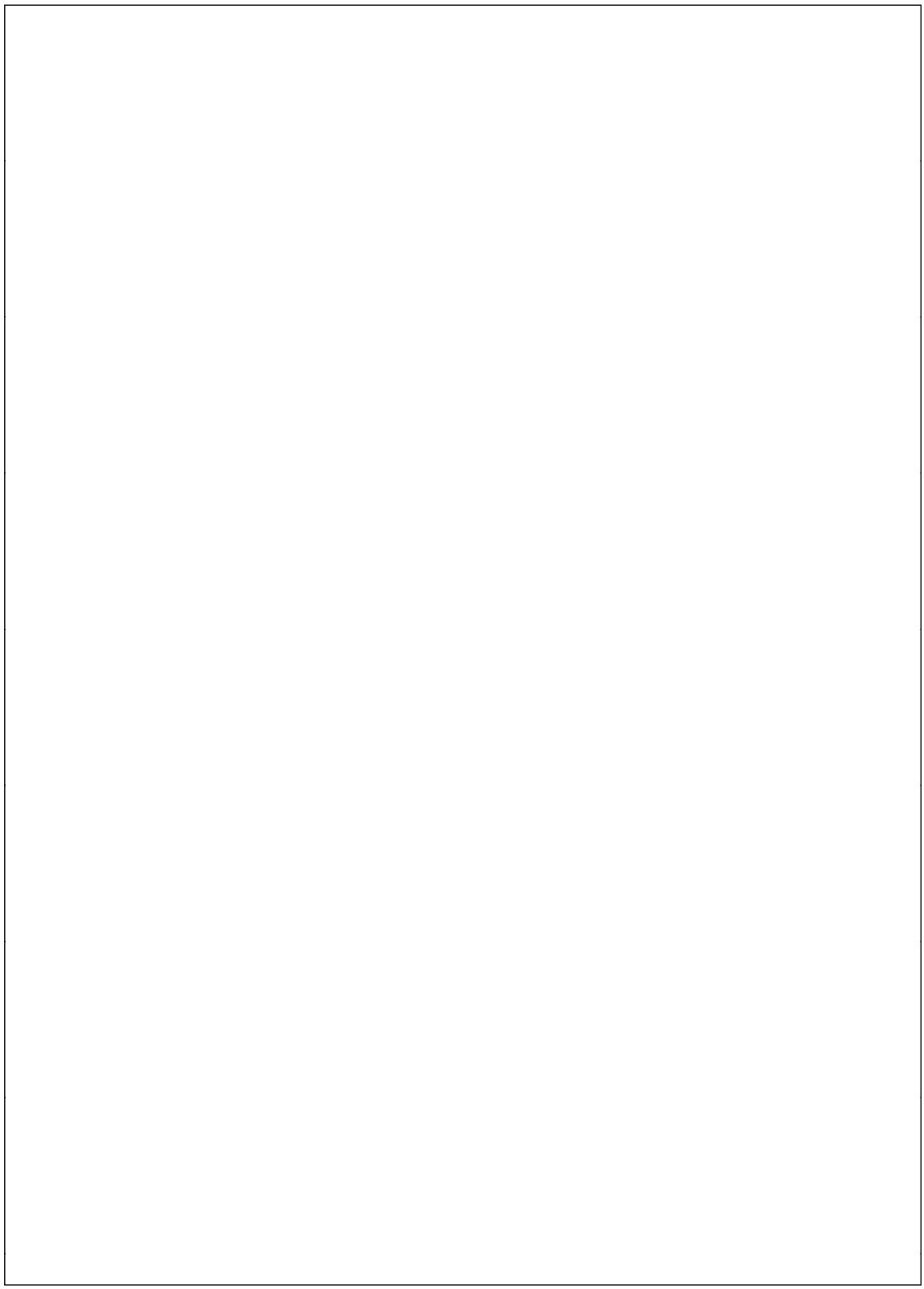
Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

Ordering Information

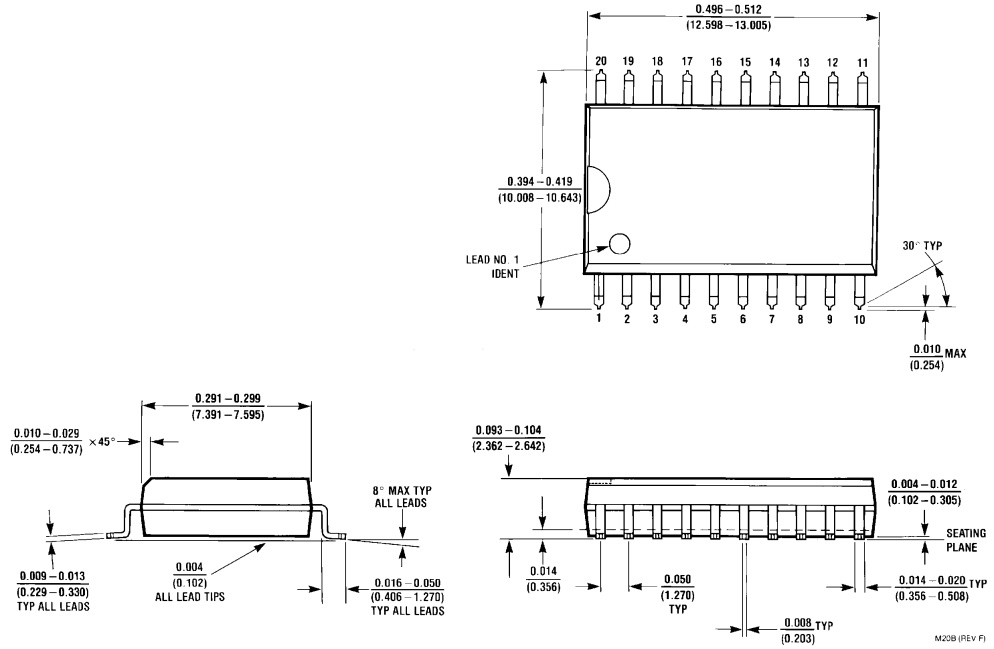
The device number is used to form part of a simplified purchasing code, where the package type and temperature range are defined as follows:



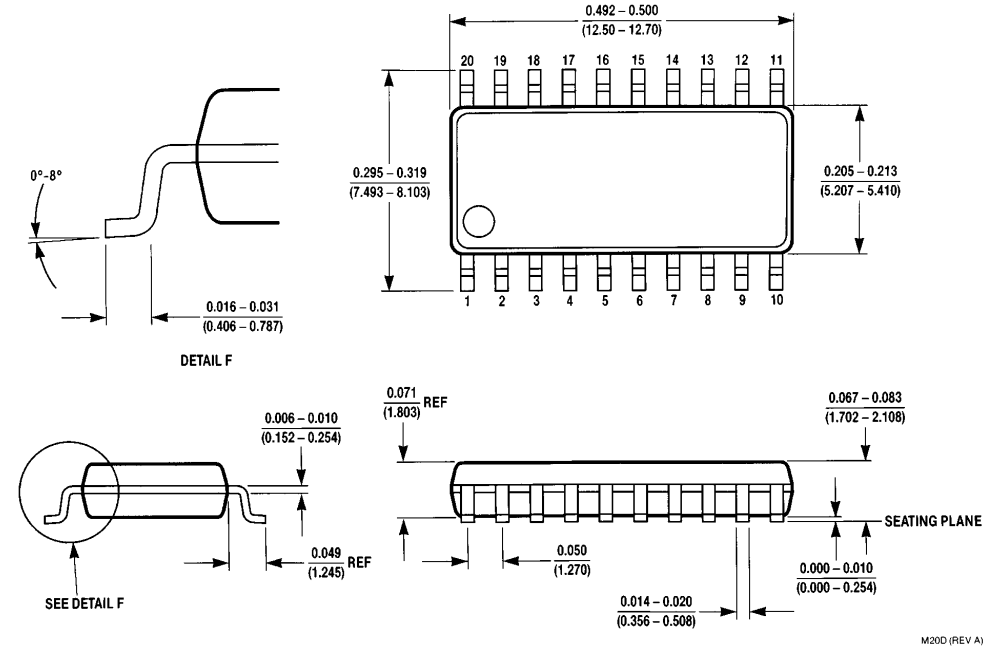
TL/F/11506–4



Physical Dimensions inches (millimeters)

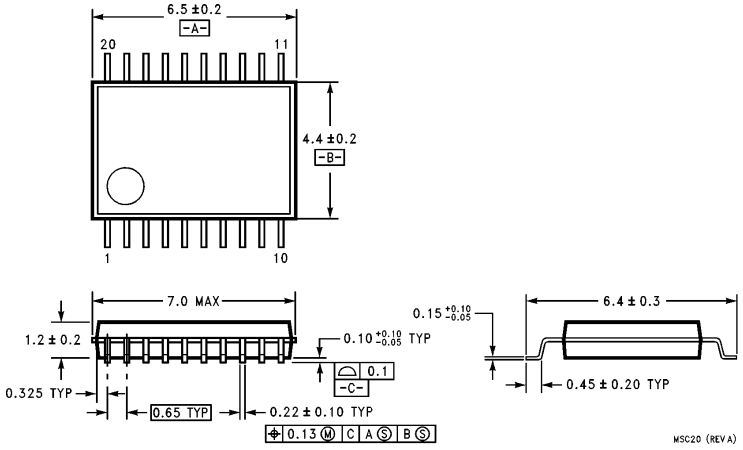


20-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Order Number 74VHC240M or 74VHC240MX
NS Package Number M20B

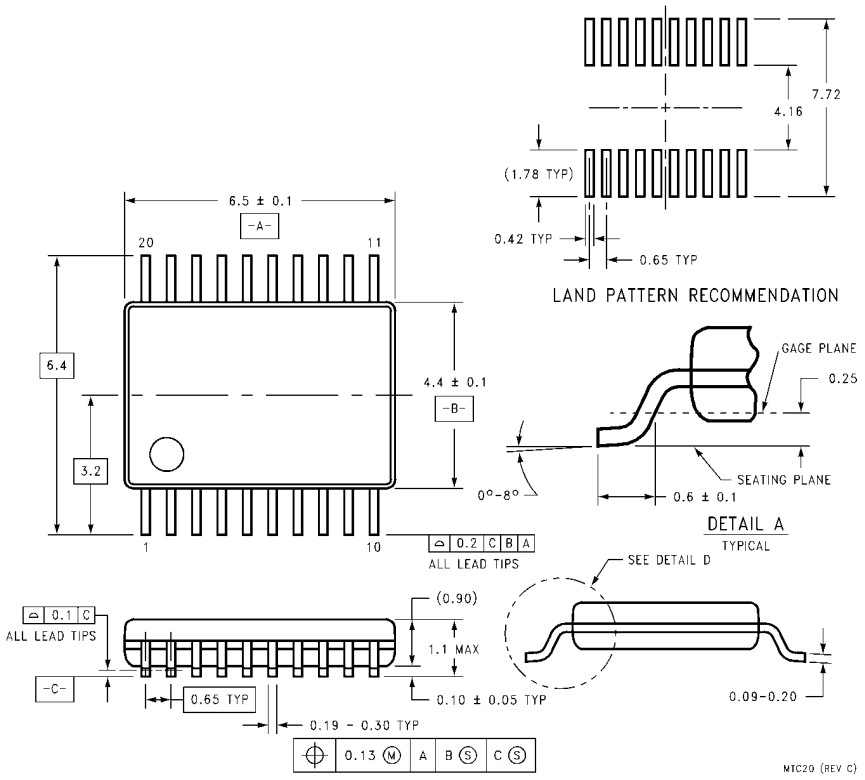


20-Lead Plastic EIAJ SOIC (SJ)
Order Number 74VHC240SJ or 74VHC240SJX
NS Package Number M20D

Physical Dimensions (millimeters) (Continued)

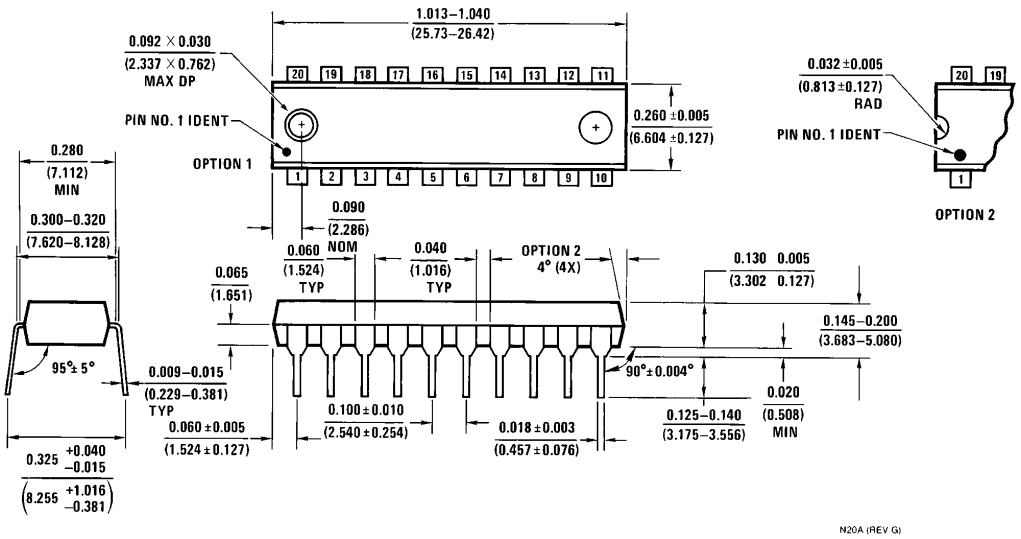


20-Lead Plastic EIAJ SSOP Type I (MSC)
Order Number 74VHC240MSCX
NS Package Number MSC20



20-Lead Plastic JEDEC TSSOP Type I (MTC)
Order Number 74VHC240MTC or 74VHC240MTCX
NS Package Number MTC20

Physical Dimensions inches (millimeters) (Continued)



20-Lead Molded DIP
Order Number 74VHC240N
NS Package Number N20A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1997
Revised March 1999

74VHCT240A
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHCT240A is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHCT240A is an inverting 3-STATE buffer having two active-LOW output enables. This device is designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up.

Note 1: Outputs in OFF-State

Features

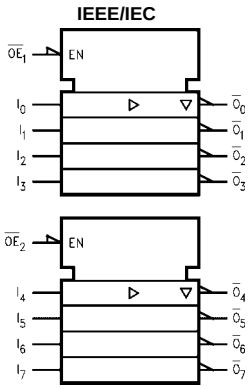
- High Speed: t_{PD} = 5.6 ns (typ) at V_{CC} = 5V
- Power down protection is provided on inputs and outputs
- Low power dissipation: I_{CC} = 4 μA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT240

Ordering Code:

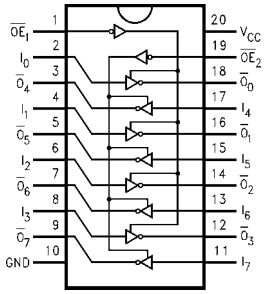
Order Number	Package Number	Package Description
74VHCT240AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT240ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT240AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT240AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs 3-STATE Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

H - HIGH Voltage Level
L - LOW Voltage Level
X - Immaterial
Z - High Impedance

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Voltage (V_{IN})	–0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	–0.5V to V_{CC} + 0.5V
(Note 4)	–0.5V to +7.0V
Input Diode Current (I_{IK})	–20 mA
Output Diode Current (I_{OK}) (Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	–65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to +5.5V
Operating Temperature (T_{OPR})	–40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = –40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = –50 μA
			3.94			3.80		V		I_{OH} = –8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
					0.36		0.44	V		I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Input = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.1	V	C_L = 50 pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	–0.9	–1.1	V	C_L = 50 pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 7: Parameter guaranteed by design.

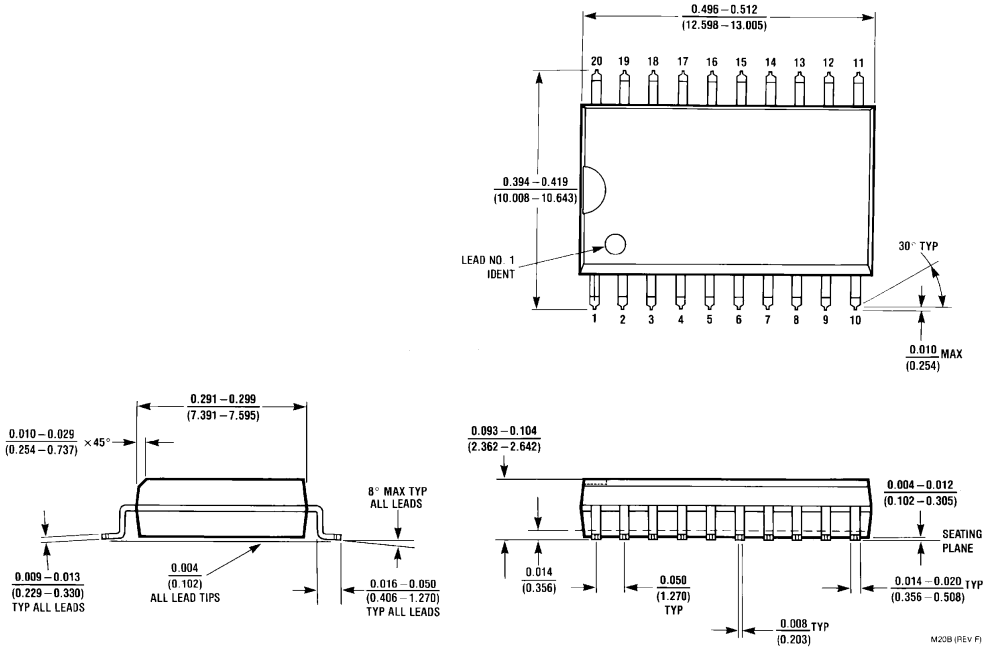
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ± 0.5		5.6	7.8	1.0	9.0	ns		$C_L = 15$ pF
t_{PHL}	Time			6.1	8.8	1.0	10.0			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		6.5	10.4	1.0	12.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			7.3	11.4	1.0	13.5			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		7.0	11.4	1.0	13.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	
t_{OSHL}	Output Skew									
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 9)	

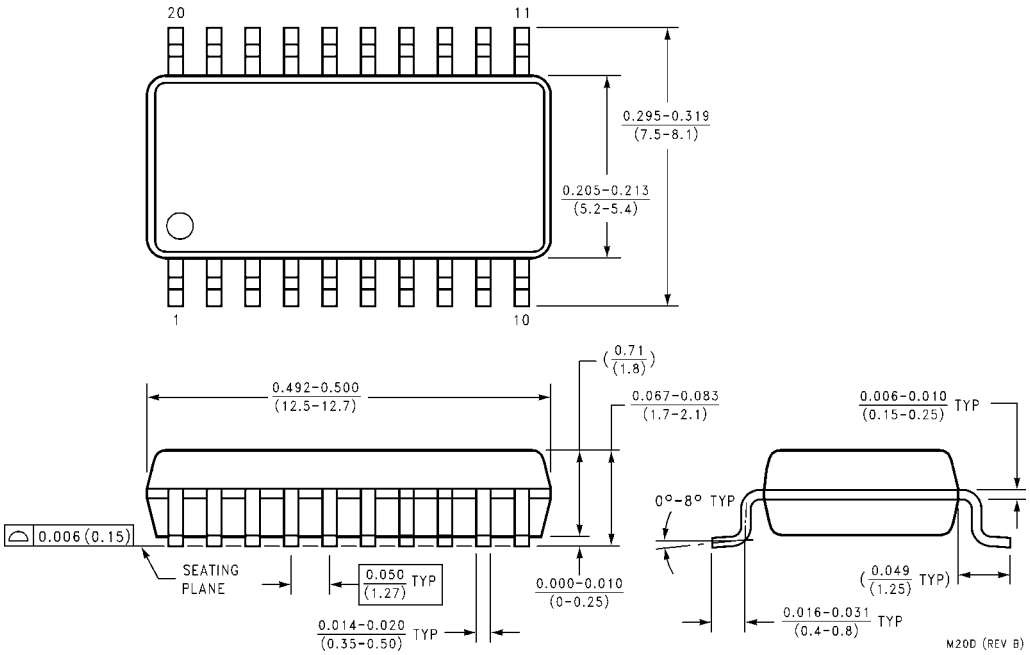
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

Physical Dimensions inches (millimeters) unless otherwise noted

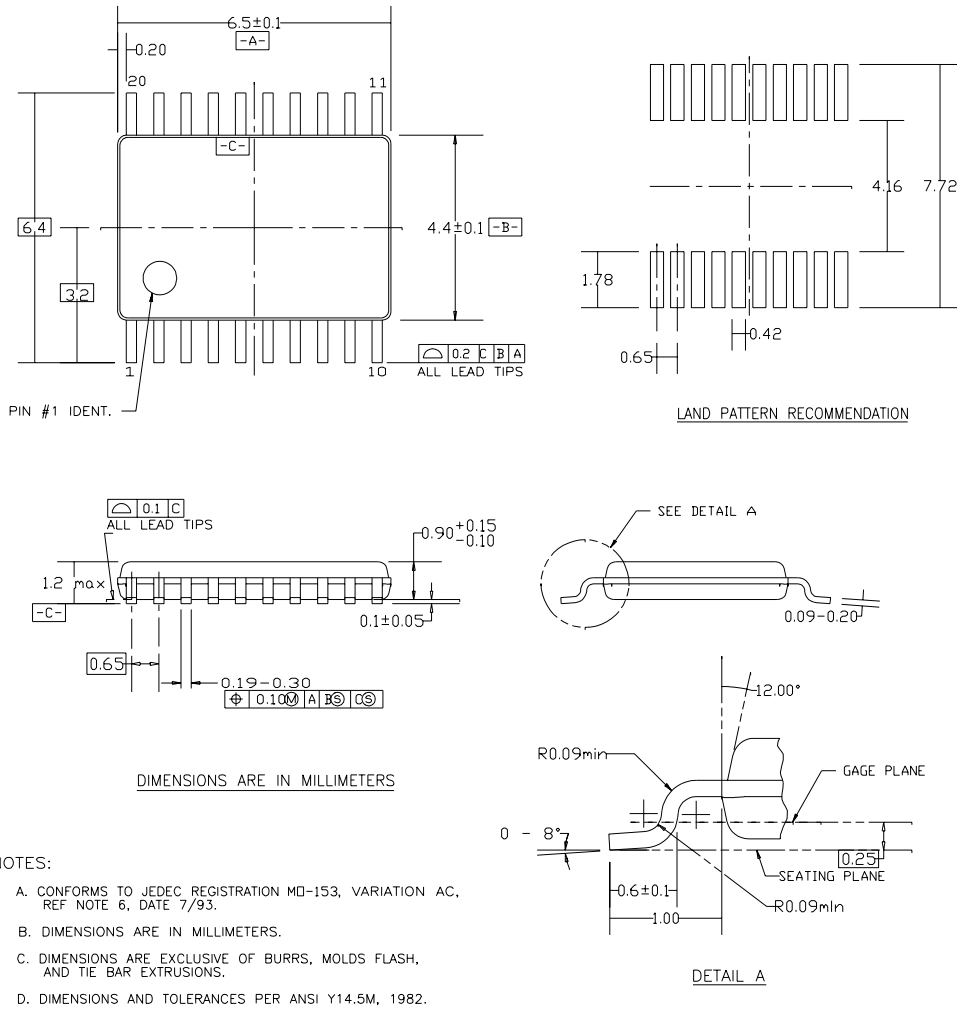


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

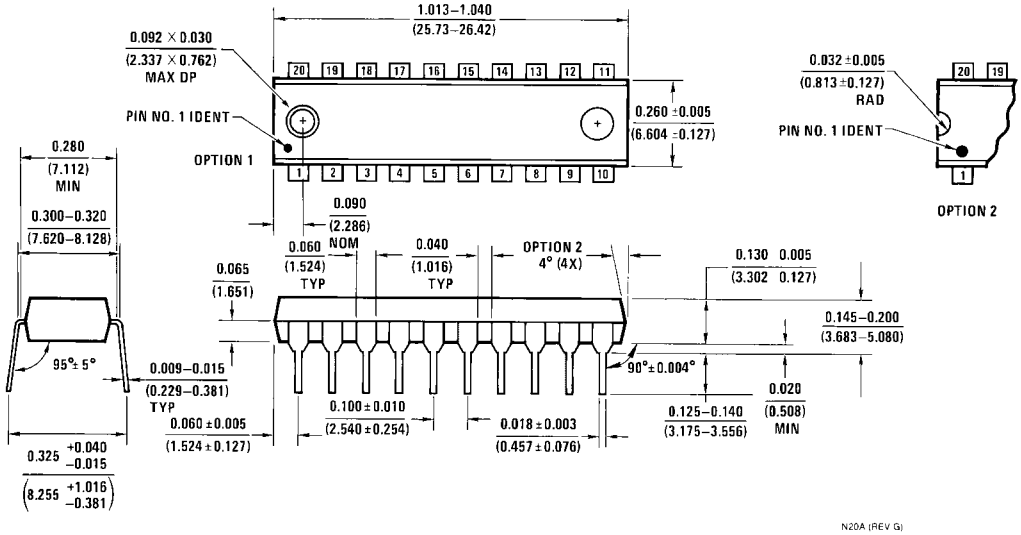
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

March 1998

74VHC244 • 74VHCT244
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHC/VHCT244 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC/VHCT244 is a non-inverting 3-STATE buffer having two active-low output enables. These devices are designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

An input protection circuit ensures that 0V–7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC t_{pd} = 3.9ns (typ) at V_{CC} = 5V
  VHCT t_{pd} = 5.4ns (typ) at V_{CC} = 5V
- High noise immunity:
  VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection:
  VHC inputs only
  VHCT inputs and outputs
- Low noise:
  VHC V_{OLP} = 0.6V (typ)
  VHCT V_{OLP} = 0.7V (typ)
- Low power dissipation:
  I_{CC} = 4 μA (max) @ T_A = 25˚C
- Pin and function compatible with 74HC/HCT244

Note 1: Add External Pull Up Resistor To VHCT Outputs To Drive CMOS Inputs

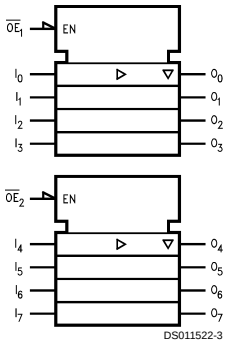
Ordering Code:

Commercial	Package Number	Package Description
74VHC244M	M20B	20-Lead Molded JEDEC SOIC
74VHC244SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC244MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHC244N	N20A	20-Lead Molded DIP
74VHCT244M	M20B	20-Lead Molded JEDEC SOIC
74VHCT244SJ	M20D	20-Lead Molded EIAJ SOIC
74VHCT244MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHCT244N	N20A	20-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

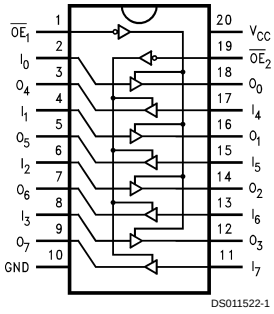
IEEE/IEC



DS011522-3

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



DS011522-1

Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
I = Immaterial
L = LOW Voltage Level
Z = High Impedance

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 3)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260˚C

Recommended Operating Conditions (Note 4)

Supply Voltage (V_{CC})	
VHC	2.0V to 5.5V
VHCT	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC Only)	0 ns/V ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: $V_{OUT} > V_{CC}$ only if output is in H or Z state.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.5			1.5				
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}		V		
V_{IL}	Low Level Input Voltage	2.0			0.5		0.5			
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}	V		
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9		V		
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1	V		
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

DC Electircal Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 5)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum High Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5 5.5	2.0 2.0			2.0 2.0		V		
V_{IL}	Low Level Input Voltage	4.5 5.5			0.8 0.8		0.8 0.8	V		
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		4.5	2.5			2.4				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V, Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage (Power Down State)	0.0			+0.5		+5.0	μA	V_{OUT} = 5.5V	

DC Electrical Characteristics for VHCT Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 6)	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	C_L = 50 pF
V_{OLV} (Note 6)	Quiet Output Minimum Dynamic V_{OL}		−0.7	−1.0	V	C_L = 50 pF
V_{IHD} (Note 6)	Minimum High Level Dynamic Input Voltage			2.0	V	C_L = 50 pF
V_{ILD} (Note 6)	Maximum High Level Dynamic Input Voltage			0.8	V	C_L = 50 pF

Note 6: Parameter guaranteed by design.

AC Electrical Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ±0.3		5.8	8.4	1.0	10.0	ns		C_L = 15 pF
t_{PHL}	Time			8.3	11.9	1.0	13.5			C_L = 50 pF
		5.0 ±0.5		3.9	5.5	1.0	6.5	ns		C_L = 15 pF
				5.4	7.5	1.0	8.5			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ±0.3		6.6	10.6	1.0	12.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			9.1	14.1	1.0	16.0			C_L = 50 pF
		5.0 ±0.5		4.7	7.3	1.0	8.5	ns		C_L = 15 pF
				6.2	9.3	1.0	10.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		10.3	14.0	1.0	16.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ±0.5		6.7	9.2	1.0	10.5			C_L = 50 pF
t_{OSLH}	Output to Output	3.3 ±0.3			1.5		1.5	ns	(Note 7)	C_L = 50 pF
t_{OSHL}	Skew	5.0 ±0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 8)	

Note 7: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

Note 8: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

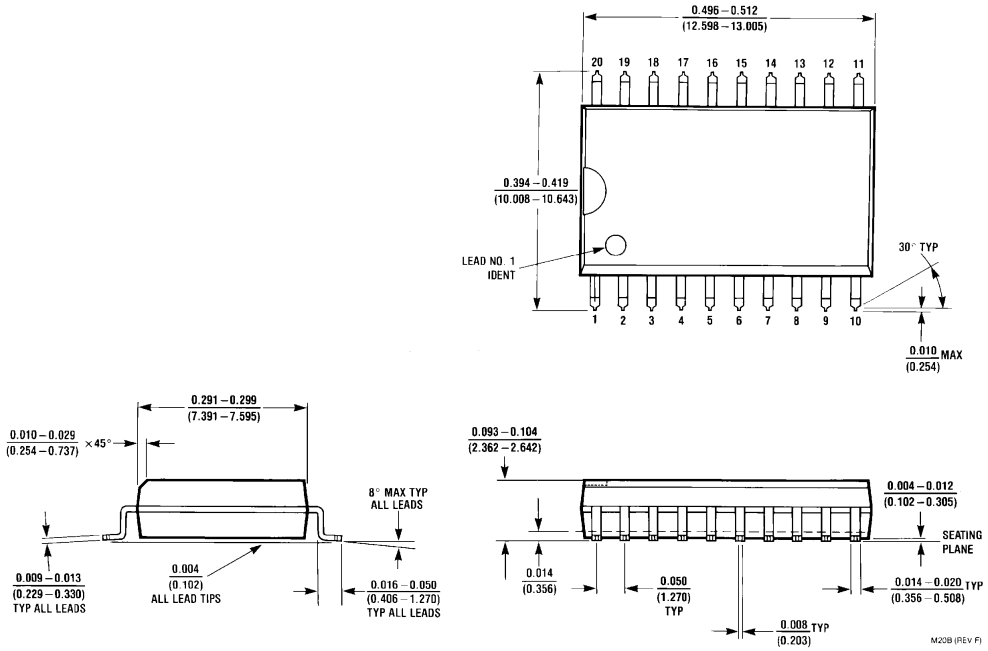
AC Electrical Characteristics for VHCT Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ±0.5		5.4	7.4	1.0	8.5	ns		C_L = 15 pF
t_{PHL}	Time			5.9	8.4	1.0	9.5			C_L = 50 pF
t_{PZL}	3-STATE Output	5.0 ±0.5		7.7	10.4	1.0	12.0	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			8.2	11.4	1.0	13.0			C_L = 50 pF
t_{PLZ} t_{PHZ}	3-STATE Output Disable Time	5.0 ±0.5		8.8	11.4	1.0	13.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{OSLH} t_{OSHL}	Output to Output Skew	5.0 ±0.5			1.0		1.0	ns	(Note 9)	C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 10)	

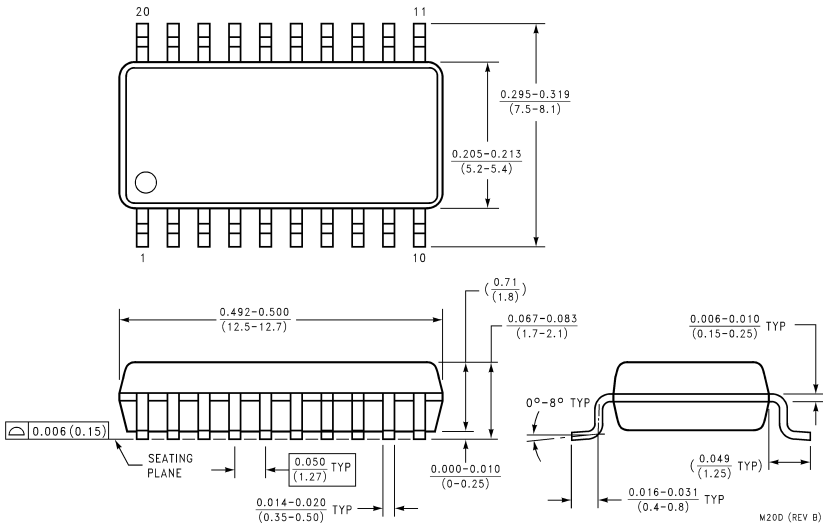
Note 9: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

Note 10: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

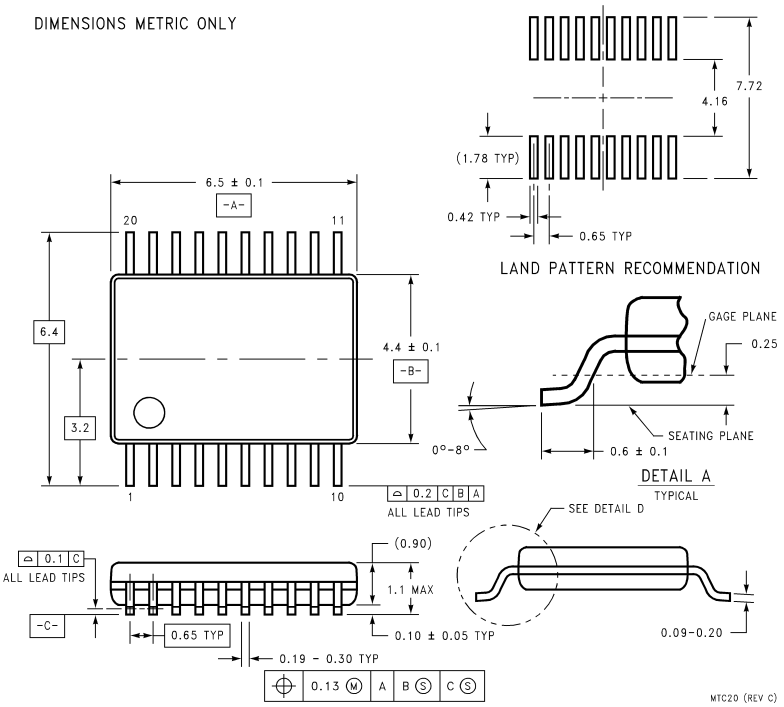


20-Lead Small Outline Integrated Circuit JEDEC SOIC (M)
Package Number M20B

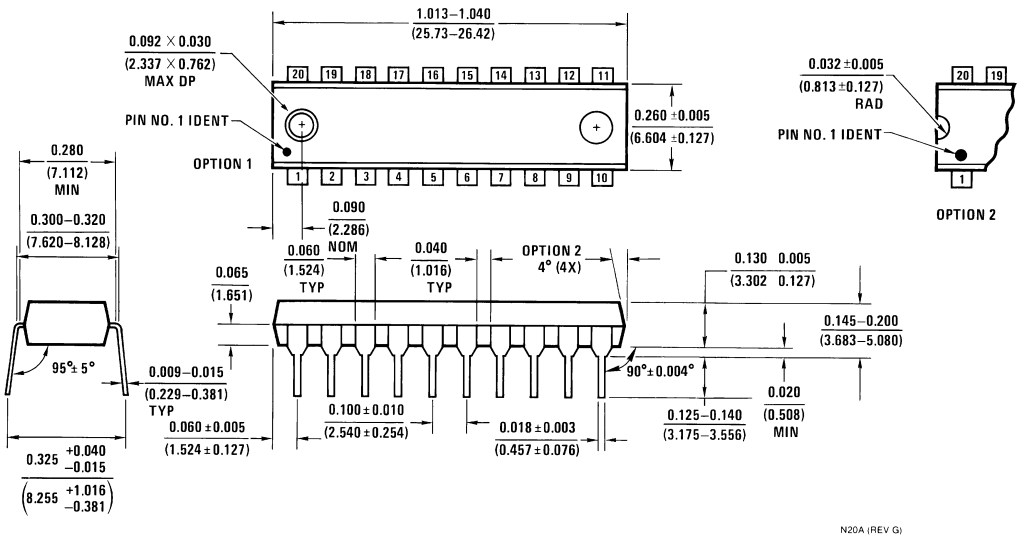


20-Lead Small Outline Integrated Circuit JEDECEIAJ SOIC (S-J)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC20



20-Lead Molded DIP
Package Number N20A

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

March 1997
Revised March 1999

74VHCT244A
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHCT244A is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHCT244A is a non-inverting 3-STATE buffer having two active-LOW output enables. This device is designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up.

Note 1: Outputs in OFF-State

Features

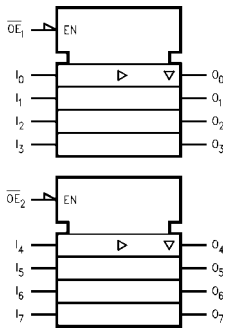
- High Speed: t_{PD} = 5.9 ns (typ) at V_{CC} = 5V
- Power down protection is provided on inputs and outputs
- Low power dissipation: I_{CC} = 4 μA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT244

Ordering Code:

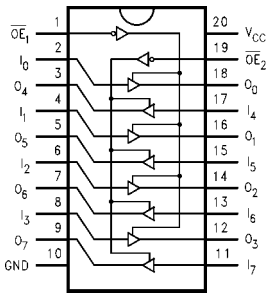
Order Number	Package Number	Package Description
74VHCT244AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT244ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT244AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT244AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
O_0–O_7	3-STATE Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	L
L	H	H
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
I = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to V_{CC} + 0.5V
(Note 4)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK}) (Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to +5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-STATE or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
			3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
					0.36		0.44	V		I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Input = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.1	V	$C_L = 50$ pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.9	−1.1	V	$C_L = 50$ pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	$C_L = 50$ pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	$C_L = 50$ pF

Note 7: Parameter guaranteed by design.

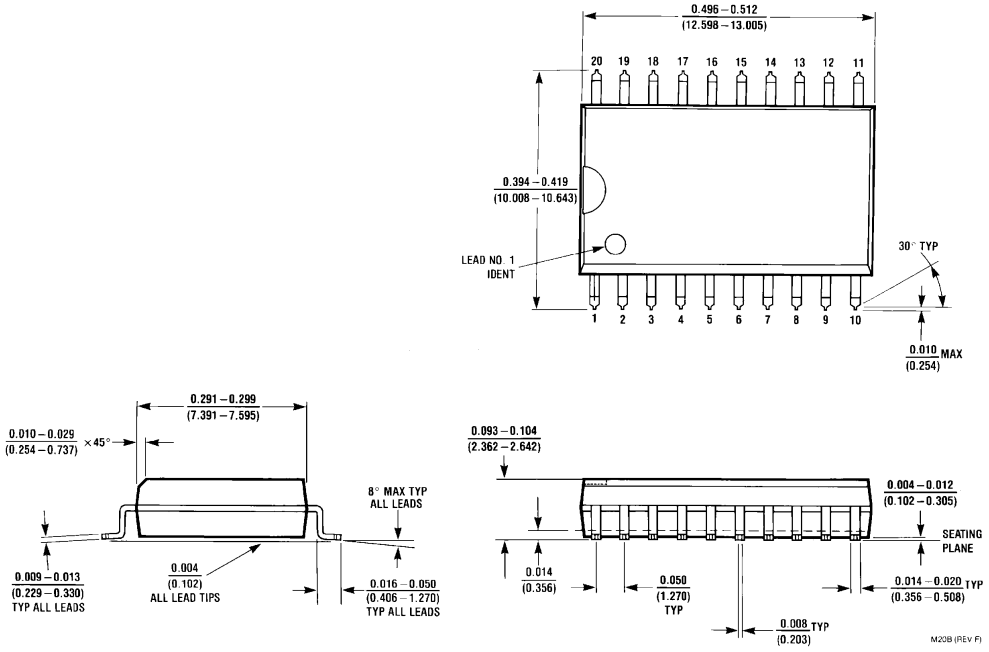
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ± 0.5		5.4	7.4	1.0	8.5	ns		$C_L = 15$ pF
t_{PHL}	Time			5.9	8.4	1.0	9.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		7.7	10.4	1.0	12.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			8.2	11.4	1.0	13.5			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		8.8	11.4	1.0	13.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	
t_{OSHL}	Output Skew									
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			18				pF	(Note 9)	

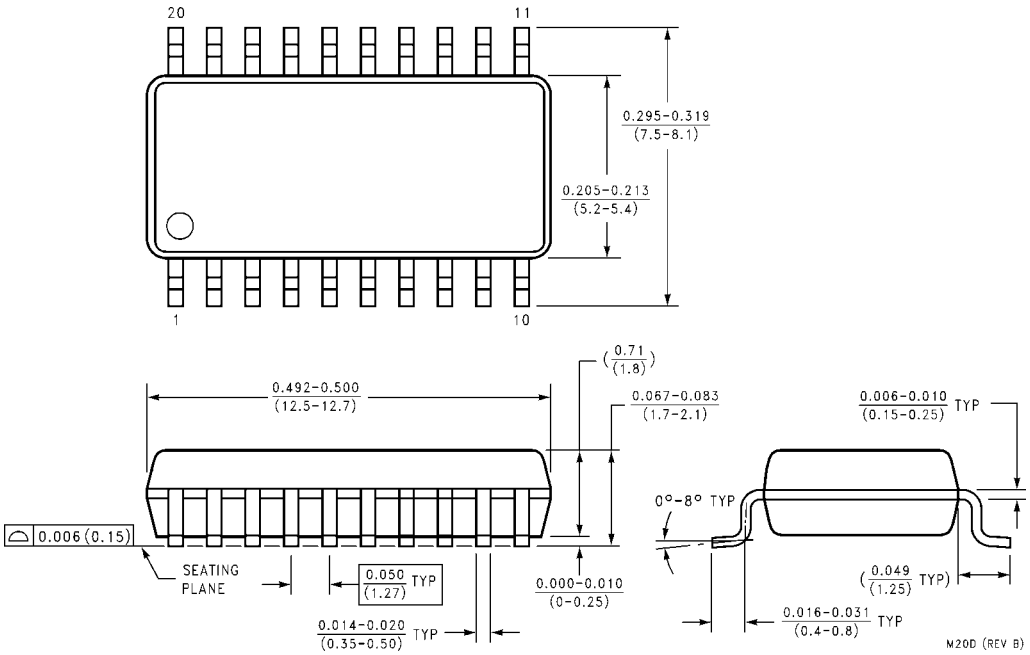
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

Physical Dimensions inches (millimeters) unless otherwise noted

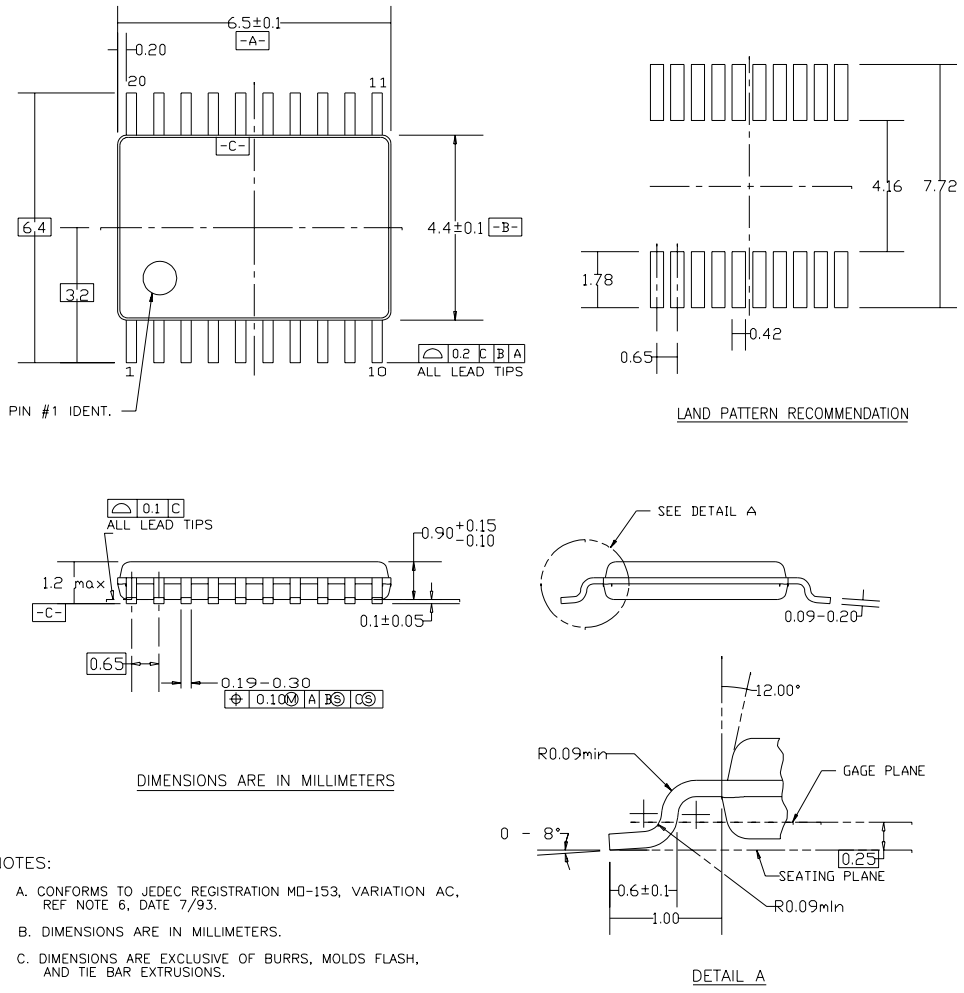


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

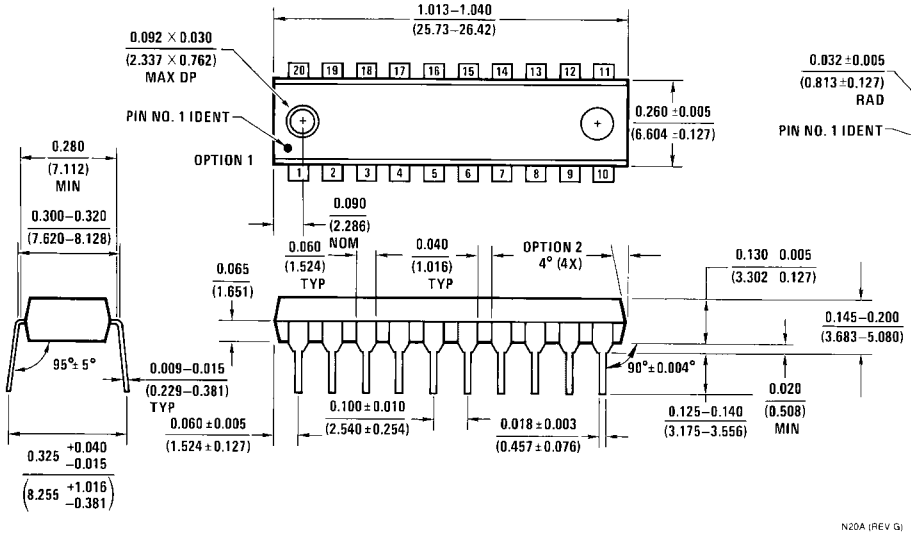
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

March 1998

FAIRCHILD SEMICONDUCTOR™

74VHC245 • 74VHCT245
Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The VHC/VHCT245 is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC245 is intended for bidirectional asynchronous communication between data busses. The direction of data transmission is determined by the level of the T/$\overline{R}$ input. The enable input can be used to disable the device so that the busses are effectively isolated. All inputs are equipped with protection circuits against static discharge.

Features

- High Speed:
  - VHC t_{pd} = 4.0 ns (typ) at V_{CC} = 5V
  - VHCT t_{pd} = 5.3 ns (typ) at V_{CC} = 5V
- High Noise Immunity:
  - VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
  - VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection:
  - VHC Inputs Only
  - VHCT Inputs and Outputs
- Low Noise:
  - VHC V_{OLP} = 0.9V (typ)
  - VHCT V_{OLP} = 1.1V (typ)
- Low Power Dissipation:
  - I_{CC} = 4 µA (Max) @ T_A = 25˚C
- Pin and Function Compatible with 74HC/HCT245

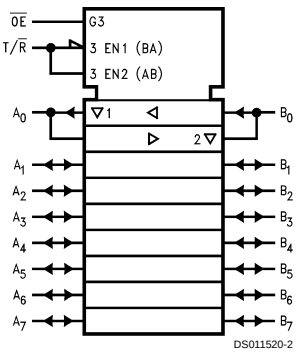
Ordering Code:

Commercial	Package Number	Package Description
74VHC245M	M20B	20 Lead Molded JEDEC SOIC
74VHC245SJ	M20D	20 Lead Molded EIAJ SOIC
74VHC245MTC	MTC20	20 Lead Molded JEDEC Type 1 TSSOP
74VHC245N	N20A	20 Lead Molded DIP
74VHCT245M	M20B	20 Lead Molded JEDEC SOIC
74VHCT245SJ	M20D	20 Lead Molded EIAJ SOIC
74VHCT245MTC	MTC20	20 Lead Molded JEDEC Type 1 TSSOP
74VHCT245N	N20A	20 Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

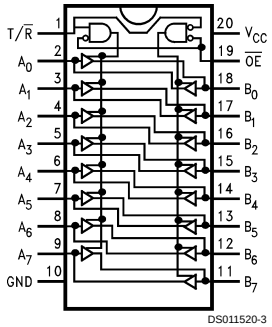
IEEE/IEC



DS011520-2

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



DS011520-3

Pin Description

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level
Any unused bus terminals during HIGH-Z State must be held HIGH or LOW.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN}) (T/$\overline{R}$, $\overline{OE}$)	−0.5V to 7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 1)	−0.5V to 7.0V
Input Diode Current (I_{IK}) (T/$\overline{R}$, $\overline{OE}$)	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260˚C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to 5.5V
VHCT (Note 1)	4.5V to 5.5V
Input Voltage (V_{IN})(T/$\overline{R}$, $\overline{OE}$)	0V to 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: V_{OUT} > V_{CC} only if output is in H or Z state.

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

DC Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IH}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9		V	or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IH}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1	V	or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{CC} or GND V_{OUT} = V_{CC} or GND V_{IN} $\overline{OE}$ = V_{IH} or V_{IL}	
I_{IN} (T/$\overline{R}$, $\overline{OE}$)	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

DC Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.9	−1.2	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

DC Characteristics for VHCT Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		4.5	2.5			2.4		V		I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		4.5			0.36		0.44	V		I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{CC} or GND V_{OUT} = V_{CC} or GND V_{IN} $\overline{OE}$ = V_{IH} or V_{IL}	
I_{IN} (T/$\overline{R}$, $\overline{OE}$)	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			+0.5		+5.0	µA	V_{OUT} = 5.5V	

DC Characteristics for VHCT Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 5)	Quiet Output Maximum Dynamic V_{OL}		1.1	1.6	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}		−1.1	−1.6	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage			2.0	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage			0.8	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ± 0.3		5.8	8.4	1.0	10.0	ns		C_L = 15 pF
t_{PHL}	Time			8.3	11.9	1.0	13.5			C_L = 50 pF
		5.0 ± 0.5		4.0	5.5	1.0	6.5	ns		C_L = 15 pF
				5.5	7.5	1.0	8.5			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ± 0.3		8.5	13.2	1.0	15.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			11.0	16.7	1.0	19.0			C_L = 50 pF
		5.0 ± 0.5		5.8	8.5	1.0	10.0	ns		C_L = 15 pF
				7.3	10.6	1.0	12.0			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ± 0.3		11.5	15.8	1.0	18.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ± 0.5		7.0	9.7	1.0	11.0			C_L = 50 pF
t_{OSLH}	Output to Output	3.3 ± 0.3			1.5		1.5	ns	(Note 6)	C_L = 50 pF
t_{OSHL}	Skew	5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN} ($T/\overline{R}$, $\overline{OE}$)	Input Capacitance			4	10		10	pF	V_{CC} = Open	
$C_{I/O}$	Output Capacitance			8				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			21				pF	(Note 7)	

Note 6: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

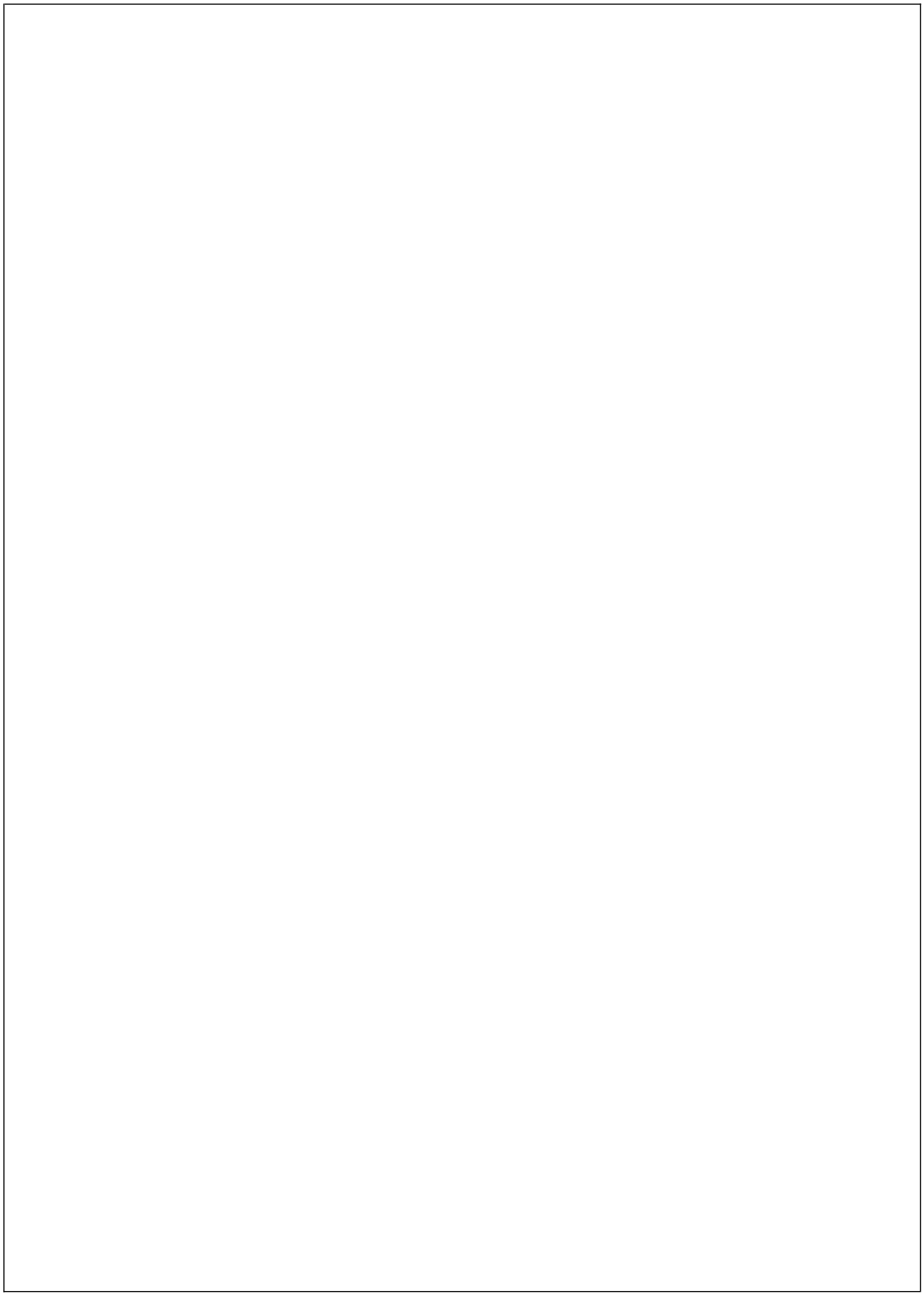
Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per Bit).

AC Electrical Characteristics for VHCT Family Devices

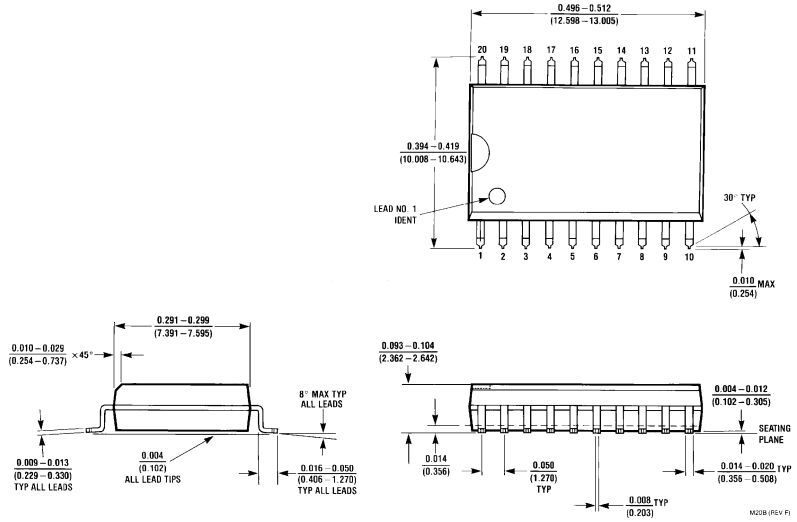
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ±0.5		4.5	7.7	1.0	8.5	ns		C_L = 15 pF
t_{PHL}	Time			5.3	8.7	1.0	9.5			C_L = 50 pF
t_{PZL}	3-STATE Output	5.0 ±0.5		8.9	13.8	1.0	15.0	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			9.7	14.8	1.0	16.0			C_L = 50 pF
t_{PLZ}	3-STATE Output	5.0 ±0.5		10.0	15.4	1.0	16.5	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to Output Skew	5.0 ±0.5			1.0		1.0	ns	(Note 8)	C_L = 50 pF
t_{OSHL}										
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
$C_{I/O}$	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			23				pF	(Note 9)	

Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

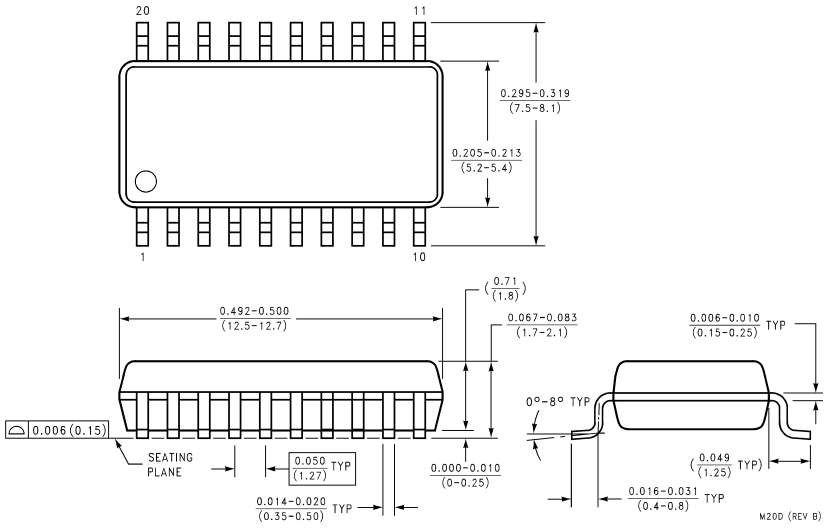
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per Bit).



Physical Dimensions inches (millimeters) unless otherwise noted

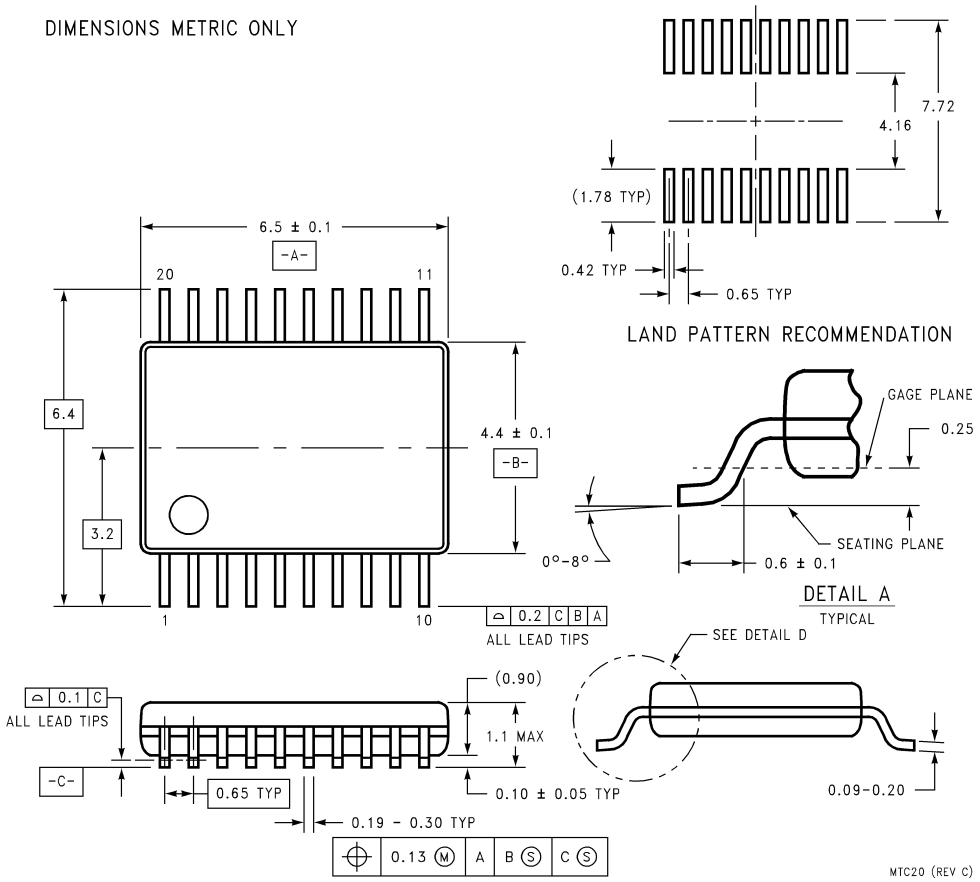


20-Lead Small Outline Package —JEDEC SOIC (M)
Package Number M20B



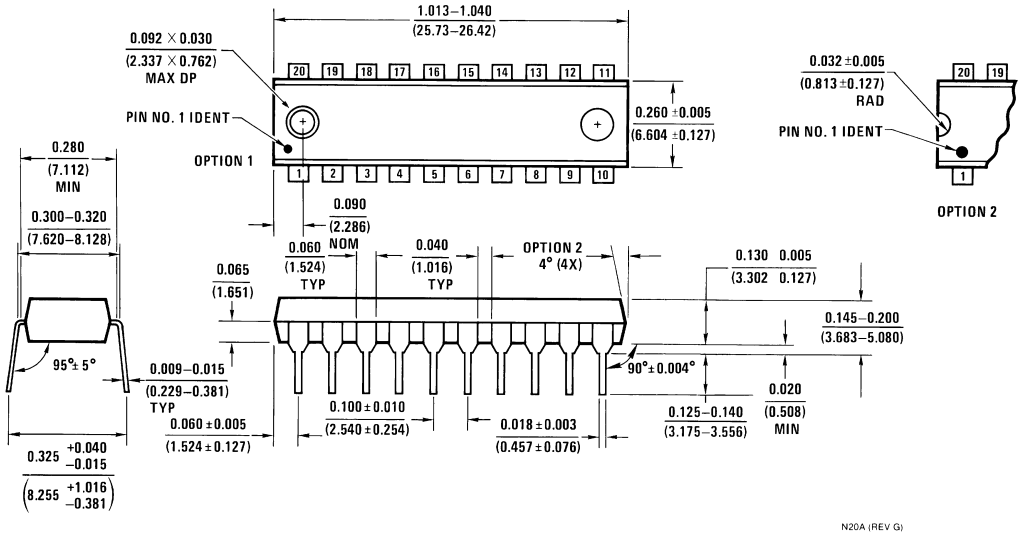
20-Lead Small Outline Package EIAJ SOIC (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.300" Wide) Molded Dual-In-Line Package
Package Number N20A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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74VHCT245A
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHCT245A is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHCT245A is intended for bidirectional asynchronous communication between data busses. The direction of data transmission is determined by the level of the T/R input. The enable input can be used to disable the device so that the busses are effectively isolated.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up.

Note 1: Outputs in OFF-State

Features

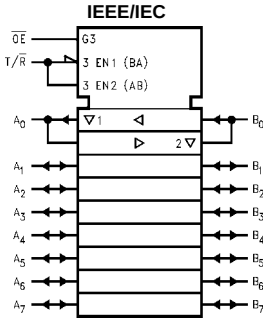
- High Speed: t_{PD} = 5.4 ns (typ) at V_{CC} = 5V
- Power Down Protection on Inputs and Outputs
- Low Power Dissipation: I_{CC} = 4 µA (Max) @ T_A = 25°C
- Pin and Function Compatible with 74HCT245

Ordering Code:

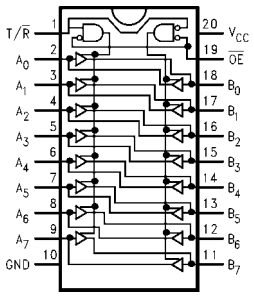
Order Number	Package Number	Package Description
74VHCT245AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT245ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT245AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT245AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}$	Output Enable Input
T/$\overline{R}$	Transmit/Receive Input
A_0–A_7	Side A Inputs or 3-STATE Outputs
B_0–B_7	Side B Inputs or 3-STATE Outputs

Truth Table

Inputs		Outputs
$\overline{OE}$	T/$\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to V_{CC} + 0.5V
(Note 4)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK}) (Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to +5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
			3.94			3.80		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
					0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Input = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	$C_L = 50$ pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	–1.2	–1.6	V	$C_L = 50$ pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	$C_L = 50$ pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	$C_L = 50$ pF

Note 7: Parameter guaranteed by design.

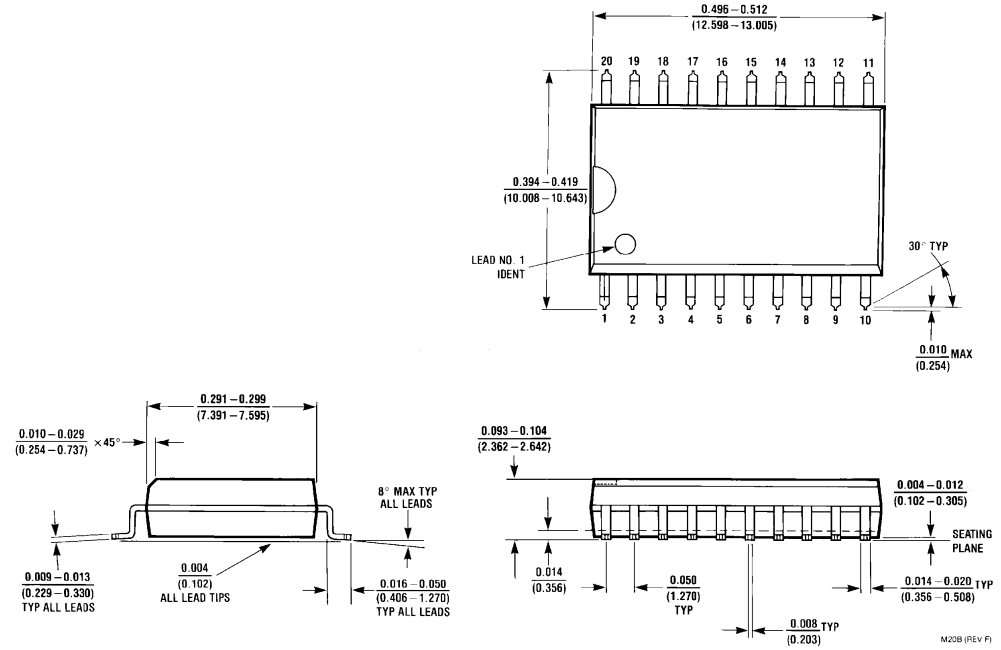
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ± 0.5		4.9	7.7	1.0	8.5	ns		$C_L = 15$ pF
t_{PHL}	Time			5.4	8.7	1.0	9.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		9.4	13.8	1.0	15.0	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			9.9	14.8	1.0	16.0			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		10.1	15.4	1.0	16.5	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	
t_{OSHL}	Output Skew									
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			13				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			16				pF	(Note 9)	

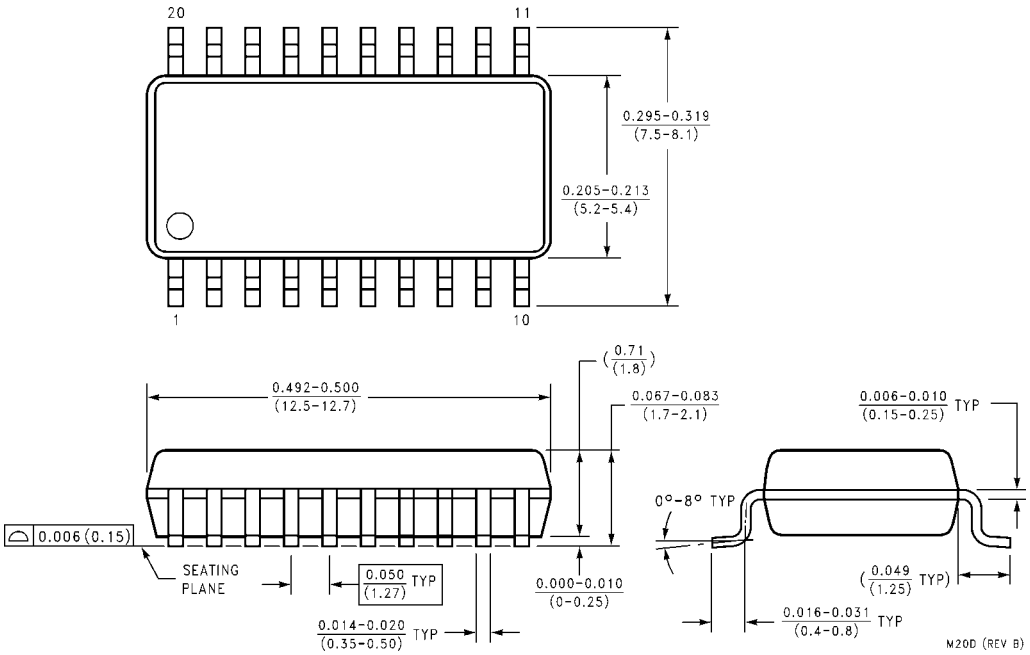
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

Physical Dimensions inches (millimeters) unless otherwise noted

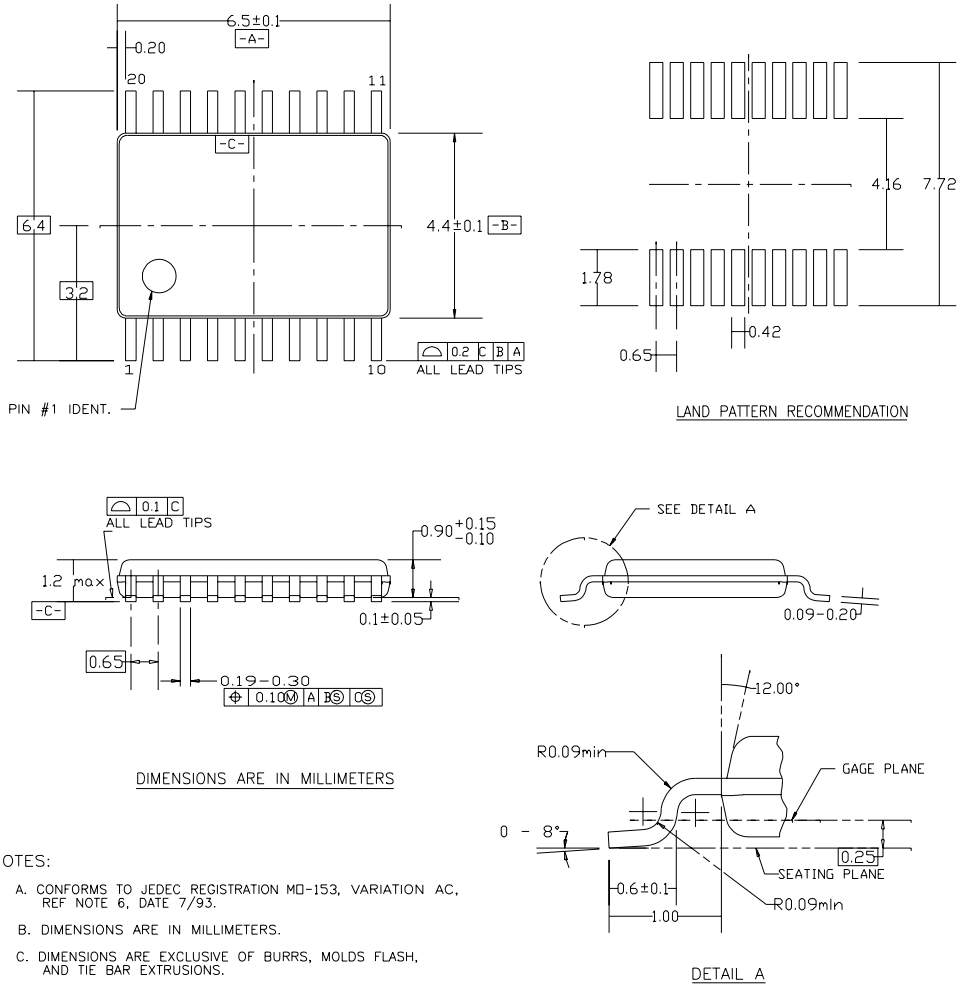


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

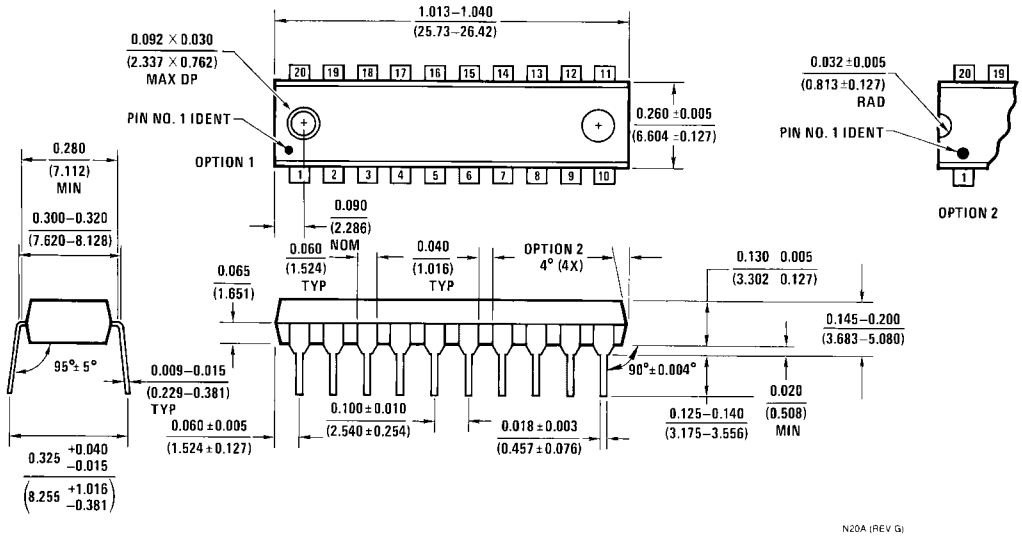
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

January 1998

74VHC373 • 74VHCT373
Octal D-Type Latch with 3-STATE Outputs

General Description

The VHC/VHCT373 is an advanced high speed CMOS octal D-type latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ($\overline{OE}$). The latches appear transparent to data when latch enable (LE) is HIGH. When LE is low, the data that meets the setup time is latched. When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V–7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC t_{pd} = 5.0 ns (typ) @ V_{CC} = 5V
  VHCT t_{pd} = 5.1 ns (typ) @ V_{CC} = 5V
- High Noise Immunity:
  VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection:
  VHC Inputs Only
  VHCT Inputs and Outputs
- Low Noise:
  VHC V_{OLP} = 0.6V (typ)
  VHCT V_{OLP} = 0.8V (typ)
- Low Power Dissipation:
  I_{CC} = 4 µA (Max) @ T_a = 25˚C
- Pin and Function Compatible with 74HC/HCT373

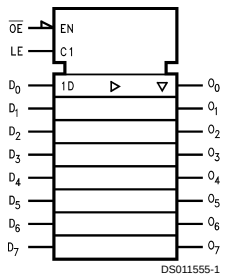
Ordering Code:

Commercial	Package Number	Package Description
74VHC373M	M20B	20-Lead Molded JEDEC SOIC
74VHC373SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC373MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHC373N	N20A	20-Lead Molded DIP
74VHCT373M	M20B	20-Lead Molded JEDEC SOIC
74VHCT373SJ	M20D	20-Lead Molded EIAJ SOIC
74VHCT373MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHCT373N	N20A	20-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

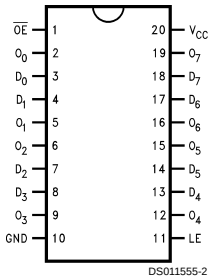
IEEE/IEC



DS011555-1

Connection Diagram

Pin Assignment for DIP,TSSOP and SOIC



DS011555-2

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

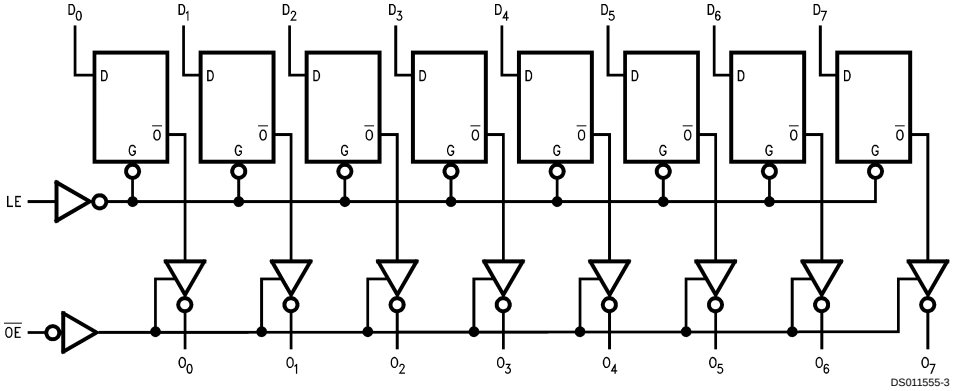
Inputs			Outputs
LE	$\overline{OE}$	D_n	O_n
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH to Low transition of Latch Enable

Functional Description

The VHC/VHCT373 contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



DS011555-3

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to + 7.0V
DC Input Voltage (V_{IN})	−0.5V to + 7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 2)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (VHC)	±20 mA
(VHCT)	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 sec)	260˚C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to + 5.5V
VHCT	4.5V to + 5.5V
Input Voltage (V_{IN})	0V to + 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	
VHC/VHCT	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ~ 100 ns/V
V_{CC} = 5.0 ±0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: $V_{OUT} > V_{CC}$ only if output is in H or Z state.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0−5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0−5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0−5.5			±0.1		±1.0	µA	V_{IN} = 5.5 or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
		4.5	2.5			2.4		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
		4.5			0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}	
									V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V	
									Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			+0.5		+0.5	μA	V_{OUT} = 5.5V	

Noise Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = +25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 5)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.8	1.2	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.2	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time (LE to O_n)	3.3 ± 0.3		7.0	11.0	1.0	13.0	ns		C_L = 15 pF
t_{PHL}				9.5	14.5	1.0	16.5			C_L = 50 pF
		5.0 ± 0.5		4.9	7.2	1.0	8.5	ns		C_L = 15 pF
				6.4	9.2	1.0	10.5			C_L = 50 pF
t_{PLH}	Propagation Delay Time (D to O_n)	3.3 ± 0.3		7.3	11.4	1.0	13.5	ns		C_L = 15 pF
t_{PHL}				9.8	14.9	1.0	17.0			C_L = 50 pF
		5.0 ± 0.5		5.0	7.2	1.0	8.5			C_L = 15 pF
				6.5	9.2	1.0	10.5			C_L = 50 pF
t_{PZL}	3-STATE	3.3 ± 0.3		7.3	11.4	1.0	13.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Output			9.8	14.9	1.0	17.0			C_L = 50 pF
	Enable Time	5.0 ± 0.5		5.5	8.1	1.0	9.5	ns		C_L = 15 pF
				7.0	10.1	1.0	11.5			C_L = 50 pF
t_{PLZ}	3-STATE Output Disable Time	3.3 ± 0.3		9.5	13.2	1.0	15.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}		5.0 ± 0.5		6.5	9.2	1.0	10.5			C_L = 50 pF
t_{OSLH}	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 6)	C_L = 50 pF
t_{OSHL}		5.0 ± 0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			27				pF	(Note 7)	

Note 6: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL}\ min|$

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per Latch). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 14 + 13n.

AC Operating Requirements for VHC

Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
$t_{W(H)}$	Minimum Pulse Width (LE)	3.3 ± 0.3	5.0			5.0		ns
		5.0 ± 0.5	5.0			5.0		
t_S	Minimum Set-Up Time	3.3 ± 0.3	4.0			4.0		ns
		5.0 ± 0.5	4.0			4.0		
t_H	Minimum Hold Time	3.3 ± 0.3	1.0			1.0		ns
		5.0 ± 0.5	1.0			1.0		

AC Electrical Characteristics for VHCT

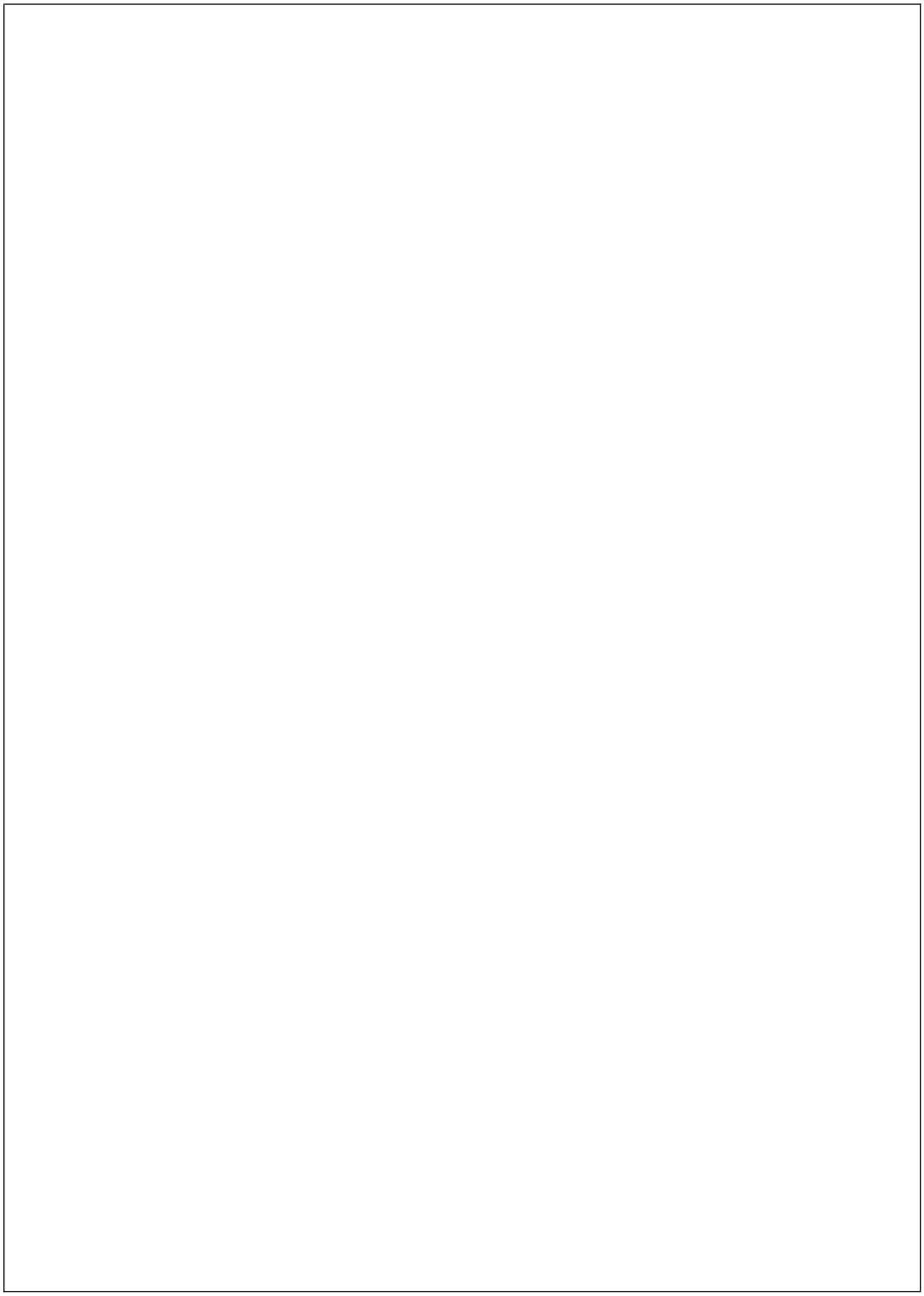
Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time (LE to O_n)	5.0 ± 0.5		7.7	12.3	1.0	13.5	ns		C_L = 15 pF
t_{PHL}				8.5	13.3	1.0	14.5			C_L = 50 pF
t_{PLH}	Propagation Delay Time (D to O_n)	5.0 ± 0.5		5.1	8.5	1.0	9.5	ns		C_L = 15 pF
t_{PHL}				5.9	9.5	1.0	10.5			C_L = 50 pF
t_{PZL}	3-STATE Output Enable Time	5.0 ± 0.5		6.3	10.9	1.0	12.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}				7.1	11.9	1.0	13.5			C_L = 50 pF
t_{PLZ}	3-STATE Output Disable Time	5.0 ± 0.5		6.8	11.2	1.0	12.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}										
t_{OSLH}	Output to Output Skew	5.0 ± 0.5			1.0		1.0		(Note 9)	
t_{OSHL}										
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			27				pF	(Note 9)	

Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

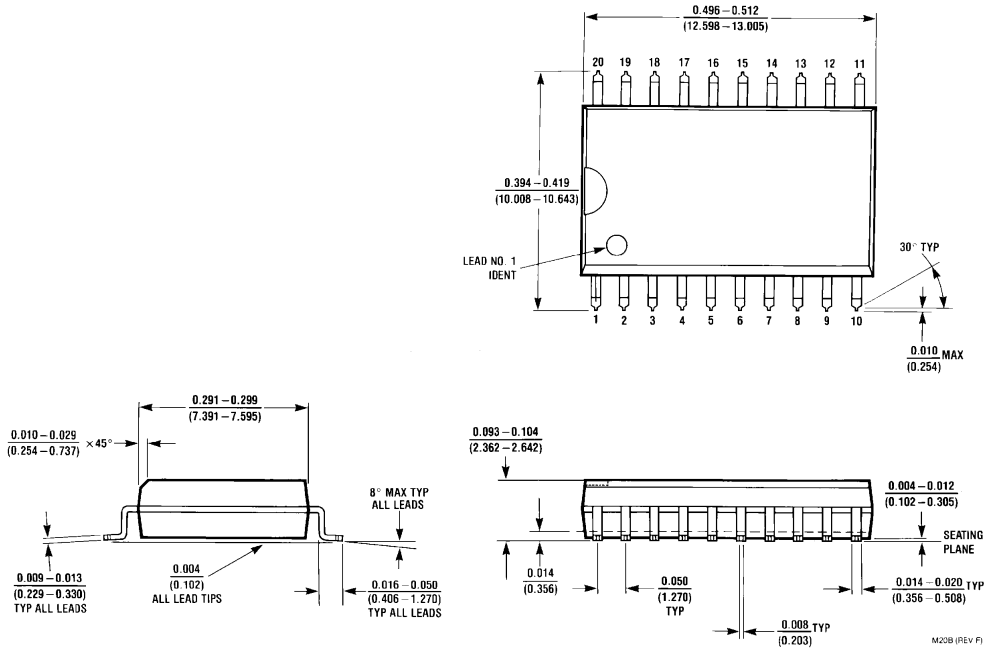
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per F/F).

AC Operating Requirements for VHCT

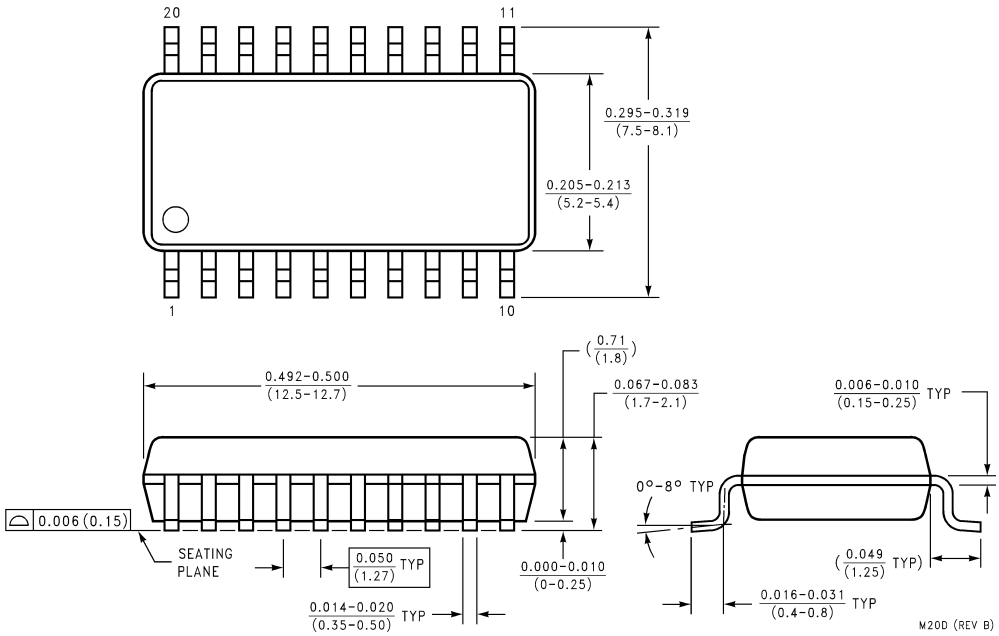
Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
$t_{W(H)}$	Minimum Pulse Width (LE)	5.0 ± 0.5	6.5			6.5		ns
t_S	Minimum Set-Up Time	5.0 ± 0.5	1.5			1.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	3.5			3.5		ns



Physical Dimensions inches (millimeters) unless otherwise noted

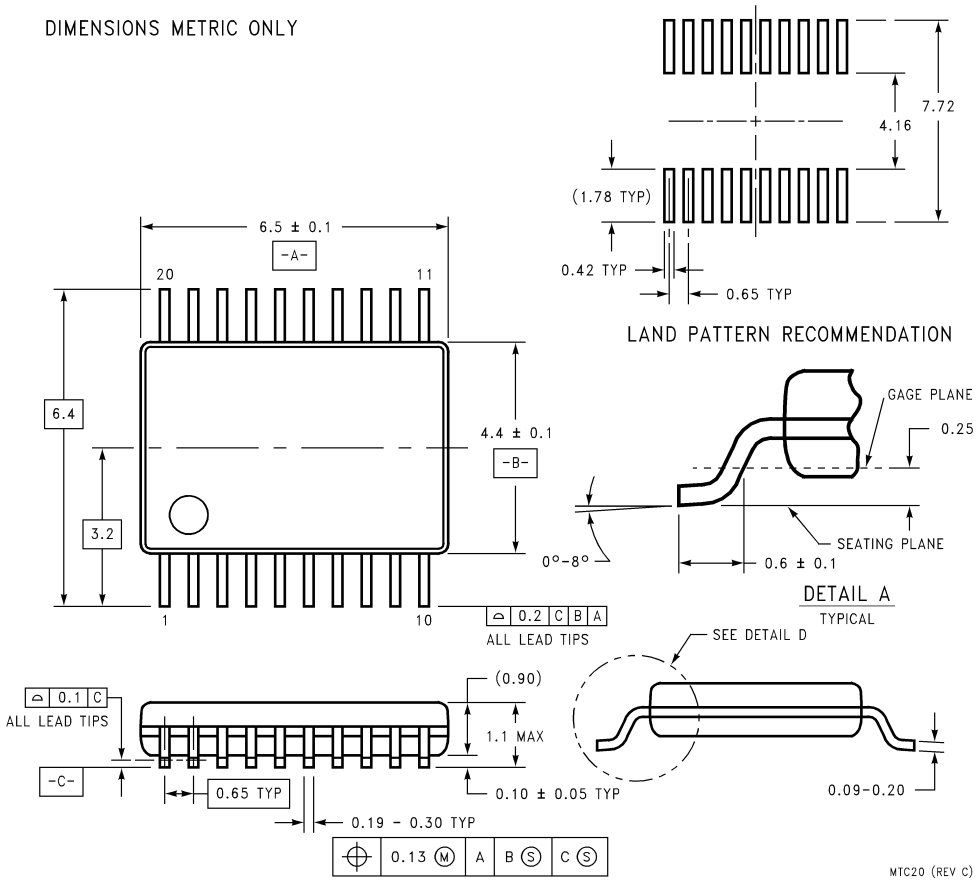


20-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Package Number M20B



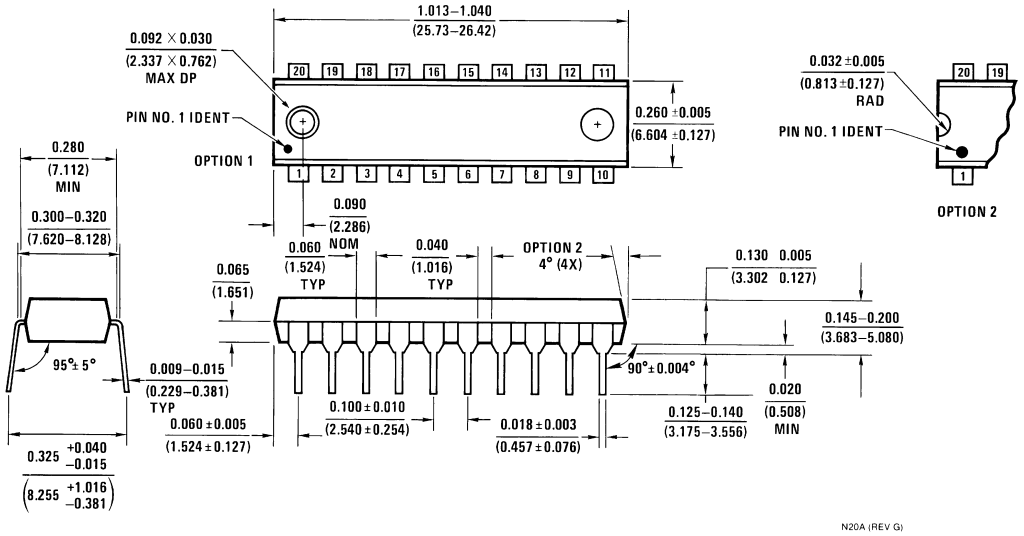
20-Lead Plastic EIAJ SOIC (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.300" Wide) Molded Dual-in-Line Package
Package Number N20A

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FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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July 1997
Revised April 1999

74VHCT373A
Octal D-Type Latch with 3-STATE Outputs

General Description

The VHCT373A is an advanced high speed CMOS octal D-type latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ($\overline{OE}$). The latches appear transparent to data when latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Note 1: Outputs in OFF-State.

Features

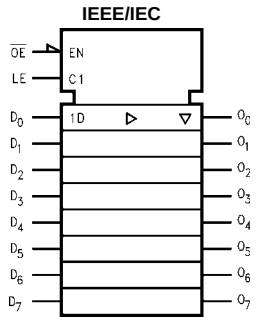
- High speed: t_{PD} = 7.7 ns (typ) at T_A = 25°C
- High Noise Immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection is provided on all inputs and outputs
- Low Power Dissipation:
  I_{CC} = 4 μA (max) @ T_A = 25°C
- Pin and Function Compatible with 74HCT373

Ordering Code:

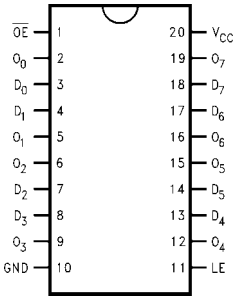
Order Number	Package Number	Package Description
74VHCT373AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT373ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT373AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT373AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

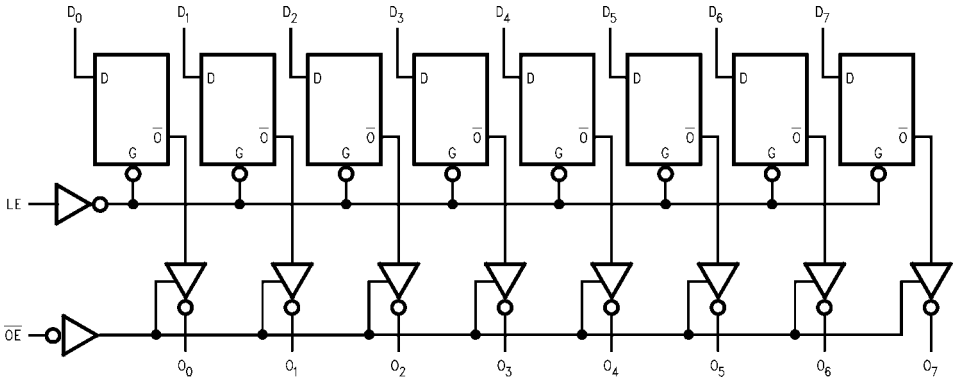
The VHCT373A contains eight D-type latches with 3-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE standard outputs are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the standard outputs are in the 2-state mode. When $\overline{OE}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
LE	**$\overline{OE}$**	**D_n**	**O_n**
X	H	X	Z
H	L	L	L
H	L	H	H
L	L	X	O_0

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to + 7.0V
DC Input Voltage (V_{IN})	−0.5V to + 7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to V_{CC} + 0.5V
(Note 4)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to + 5.5V
Input Voltage (V_{IN})	0V to + 5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0 ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		4.5	3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		4.5			0.36		0.44	V		I_{OL} = 8 mA
I_{OZ}	3-STATE Output OFF-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			+0.5		+0.5	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	C_L = 50 pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.2	−1.6	V	C_L = 50 pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 7: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time	5.0 ± 0.5		7.7	12.3	1.0	13.5	ns		$C_L = 15$ pF
t_{PHL}	(LE to O_n)			8.5	13.3	1.0	14.5			$C_L = 50$ pF
t_{PLH}	Propagation Delay Time	5.0 ± 0.5		5.1	8.5	1.0	9.5	ns		$C_L = 15$ pF
t_{PHL}	(D to O_n)			5.9	9.5	1.0	10.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output Enable Time	5.0 ± 0.5		6.3	10.9	1.0	12.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}				7.1	11.9	1.0	13.5			$C_L = 50$ pF
t_{PLZ}	3-STATE Output Disable Time	5.0 ± 0.5		8.8	11.2	1.0	12.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}										
t_{OSLH}	Output to Output Skew	5.0 ± 0.5			1.0		1.0		(Note 8)	
t_{OSHL}										
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			25				pF	(Note 9)	

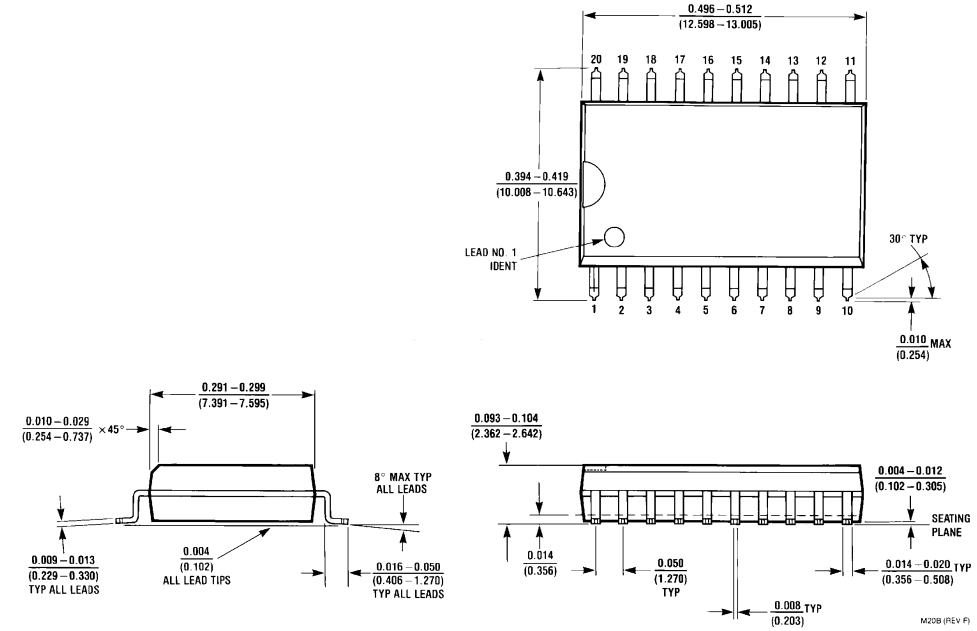
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per F/F).

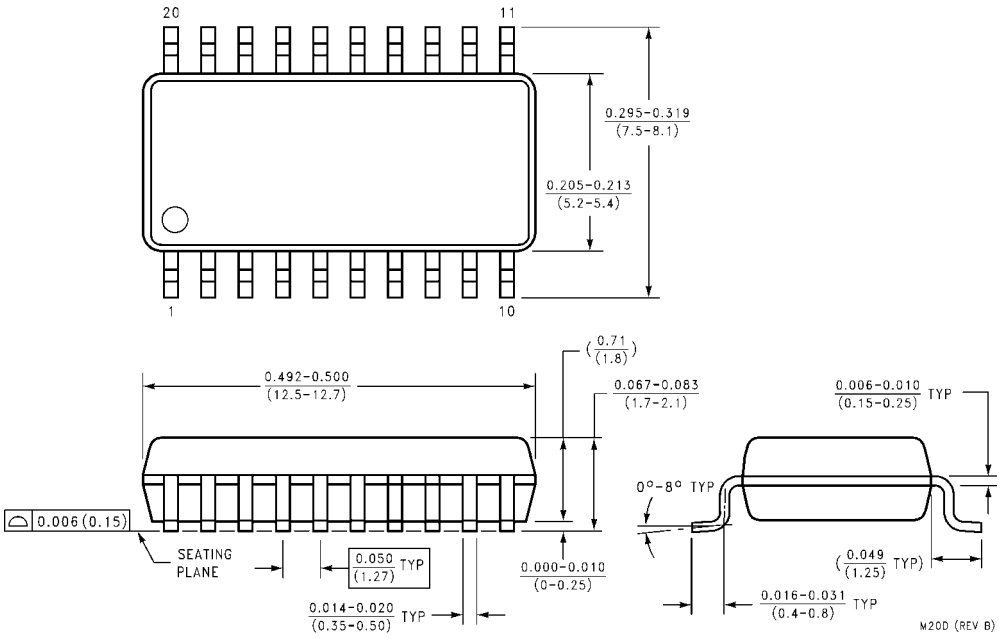
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
t_W(H)	Minimum Pulse Width (LE)	5.0 ± 0.5	6.5			8.5		ns
t_S	Minimum Set-Up Time	5.0 ± 0.5	1.5			1.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	3.5			3.5		ns

Physical Dimensions inches (millimeters) unless otherwise noted

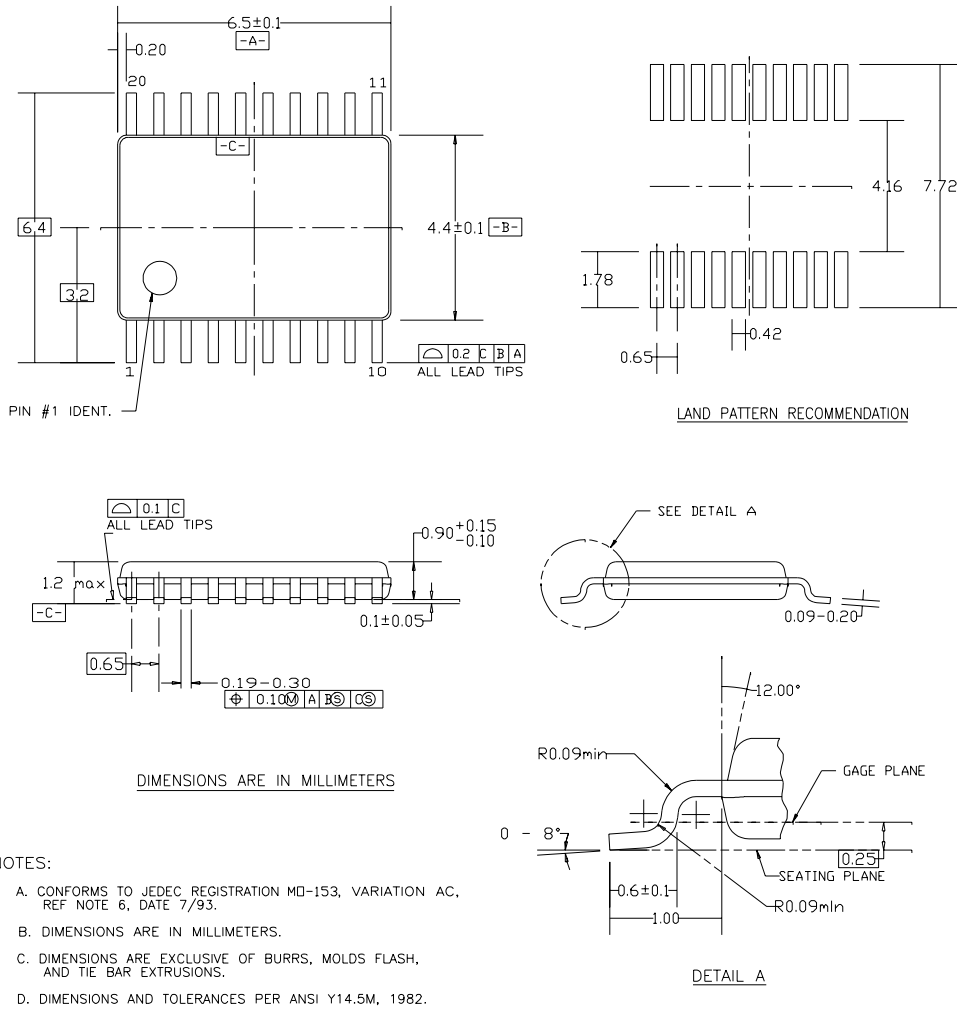


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

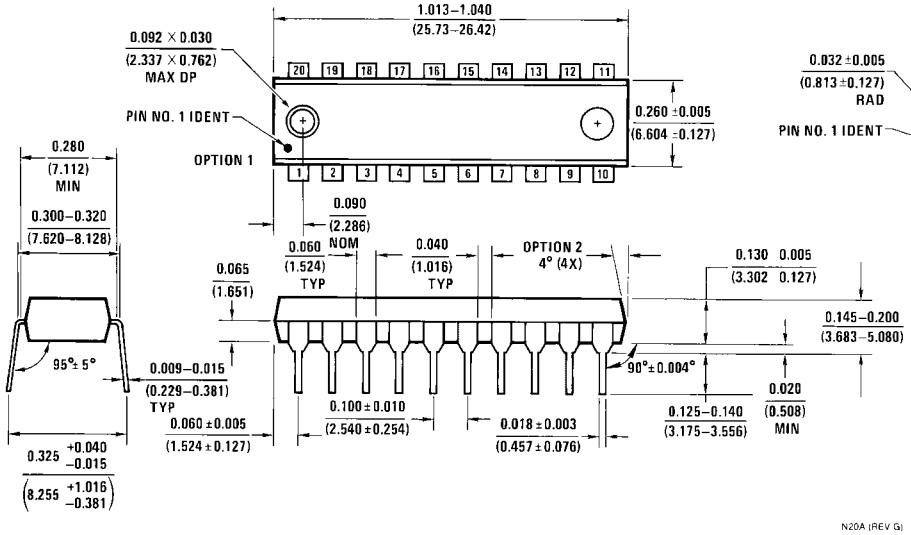
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

February 1998

FAIRCHILD SEMICONDUCTOR™

74VHC374 • 74VHCT374
Octal D Flip-Flop with 3-STATE Outputs

General Description

The VHC/VHCT374 is an advanced high speed CMOS octal flip-flop with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type flip-flop is controlled by a clock input (CP) and an output enable input ($\overline{OE}$). When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V–7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC t_{pd} = 5.4 ns (typ) at V_{CC} = 5V
  VHCT t_{pd} = 6.4 ns (typ) at V_{CC} = 5V
- High noise immunity:
  VHC $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection:
  VHC inputs only
  VHCT inputs and outputs
- Low power dissipation:
  I_{CC} = 4 μA (Max) @ T_A = 25°C
- Pin and function compatible with 74HC/HCT374

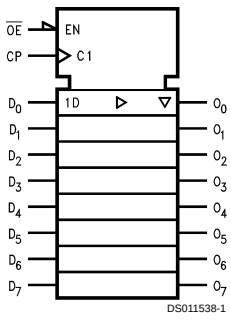
Ordering Code:

Commercial	Package Number	Package Description
74VHC374M	M20B	20-Lead Molded JEDEC SOIC
74VHC374SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC374MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHC374N	N20A	20-Lead Molded DIP
74VHCT374M	M20B	20-Lead Molded JEDEC SOIC
74VHCT374SJ	M20D	20-Lead Molded EIAJ SOIC
74VHCT374MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHCT374N	N20A	20-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

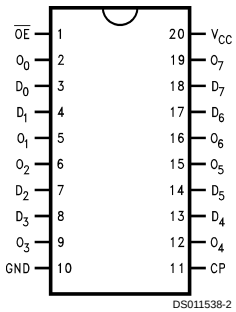
IEEE/IEC



DS011538-1

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



DS011538-2

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

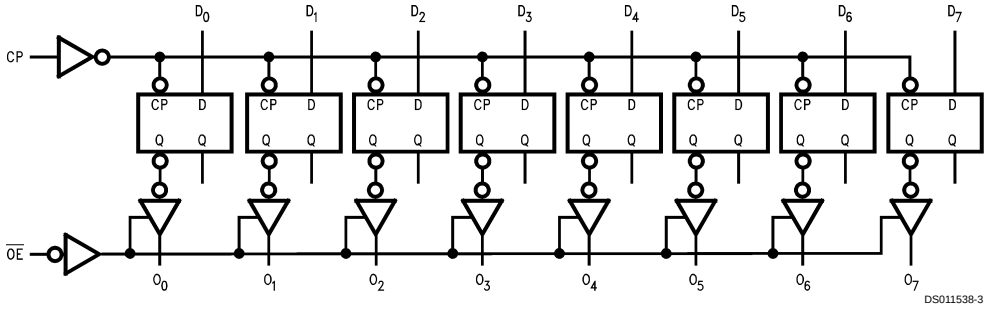
Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance
⌐ = LOW-to-HIGH Transition

Functional Description

The VHC/VHCT374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 1)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (VHC)	±20 mA
(VHCT)	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260˚C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to +5.5V
VHCT	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ns/V – 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ns/V – 20 ns/V

Note 1: V_{OUT} > V_{CC} only if output is in H or Z state.

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IH}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9		V	or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IH}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1	V	or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
									V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.6	0.9	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.6	−0.9	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$			$T_A = -40^\circ C$ to $+85^\circ C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	$V_{IN} = V_{IH}$	I_{OH} = −50 μA
			2.5			2.4		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	$V_{IN} = V_{IH}$	I_{OL} = −50 μA
					0.36		0.44	V	or V_{IL}	I_{OL} = −8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	$V_{IN} = V_{CC}$ or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			±0.5		+5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 5)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.8	1.2	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.2	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time (CP to O_n)	3.3 ±0.3		8.1	12.7	1.0	15.0	ns		C_L = 15 pF
t_{PHL}				10.6	16.2	1.0	18.5			C_L = 50 pF
		5.0 ±0.5		5.4	8.1	1.0	9.5	ns		C_L = 15 pF
				6.9	10.1	1.0	11.5			C_L = 50 pF
t_{PZL}	3-STATE Output Enable Time	3.3 ±0.3		7.1	11.0	1.0	13.0	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}				9.6	14.5	1.0	16.5			C_L = 50 pF
		5.0 ±0.5		5.1	7.6	1.0	9.0	ns		C_L = 15 pF
				6.6	9.6	1.0	11.0			C_L = 50 pF
t_{PLZ}	3-STATE Output Disable Time	3.3 ±0.3		10.2	14.0	1.0	16.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}		5.0 ±0.5		6.1	8.8	1.0	10.0			C_L = 50 pF
t_{OSLH}	Output to Output Skew	3.3 ±0.3			1.5		1.5	ns	(Note 6)	C_L = 50 pF
t_{OSHL}		5.0 ±0.5			1.0		1.0			C_L = 50 pF
f_{max}	Maximum Clock Frequency	3.3 ±0.3	80	130		70		MHz		C_L = 15 pF
			55	85		50				C_L = 50 pF
		5.0 ±0.5	130	185		110				C_L = 15 pF
			85	120		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			32				pF	(Note 7)	

Note 6: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

AC Operating Requirements for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
$t_{W(H)}$	Minimum Pulse Width (CP)	3.3 ±0.3	5.0			5.5		ns	
$t_{W(L)}$		5.0 ±0.5	5.0			5.0			
t_S	Minimum Set-Up Time	3.3 ±0.3	4.5			4.5		ns	
		5.0 ±0.5	3.0			3.0			
t_H	Minimum Hold Time	3.3 ±0.3	2.0			2.0			
		5.0 ±0.5	2.0			2.0			

AC Electrical Characteristics for VHCT

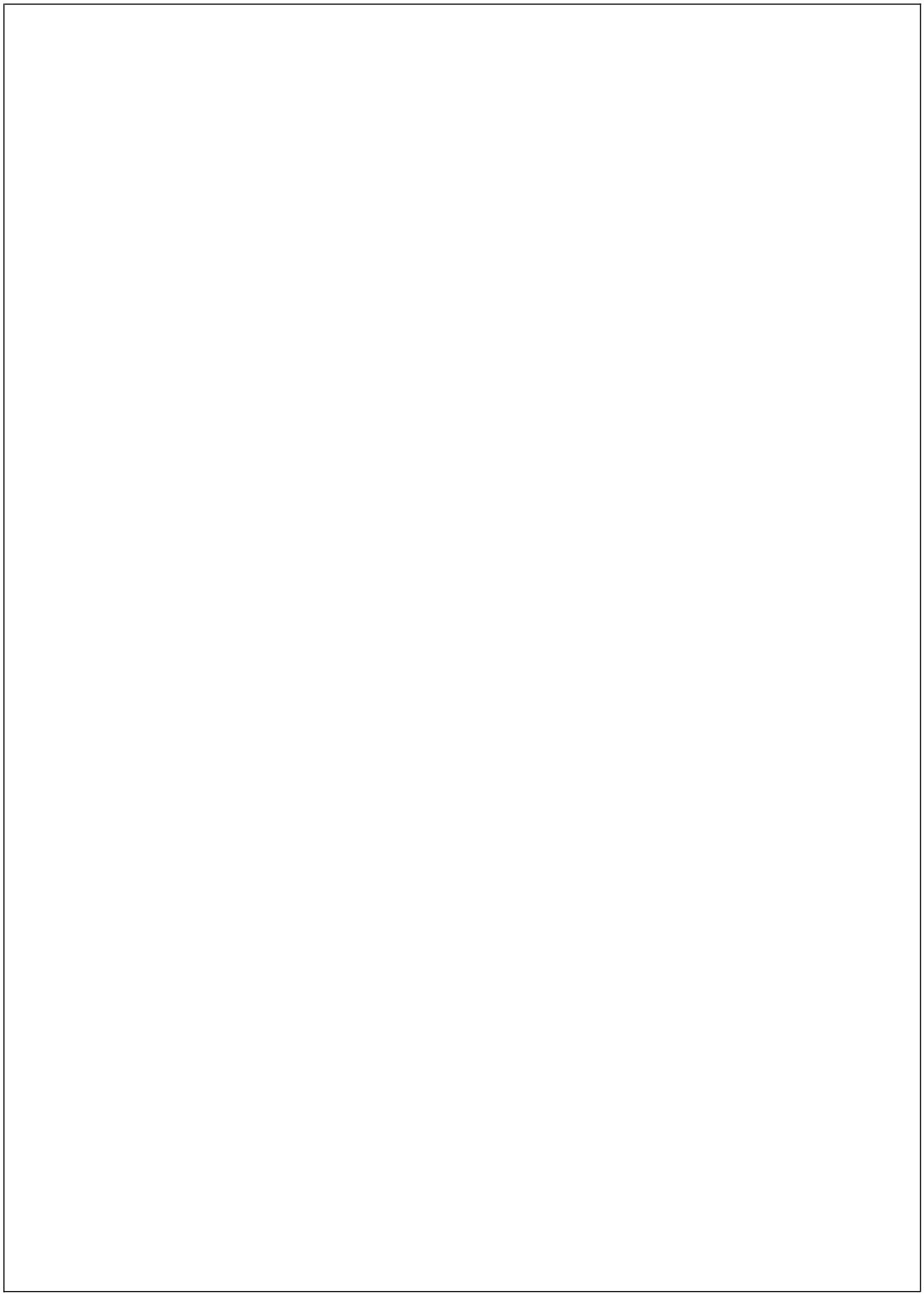
Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time	5.0 ± 0.5		5.6	9.4	1.0	10.5	ns		C_L = 15 pF
t_{PHL}				6.4	10.4	1.0	11.5			C_L = 50 pF
t_{PZL}	3-STATE Output Enable Time	5.0 ± 0.5		6.5	10.2	1.0	11.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}				7.3	11.2	1.0	12.5			C_L = 50 pF
t_{PLZ}	3-STATE Output Disable Time	5.0 ± 0.5		7.0	11.2	1.0	12.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}										
t_{OSLH}	Output to Output Skew	5.0 ± 0.5			1.0		1.0		(Note 8)	
t_{OSHL}										
f_{max}	Maximum Clock Frequency	5.0 ± 0.5	90	140		80		MHz		C_L = 15 pF
			85	130		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			27				pF	(Note 9)	

Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

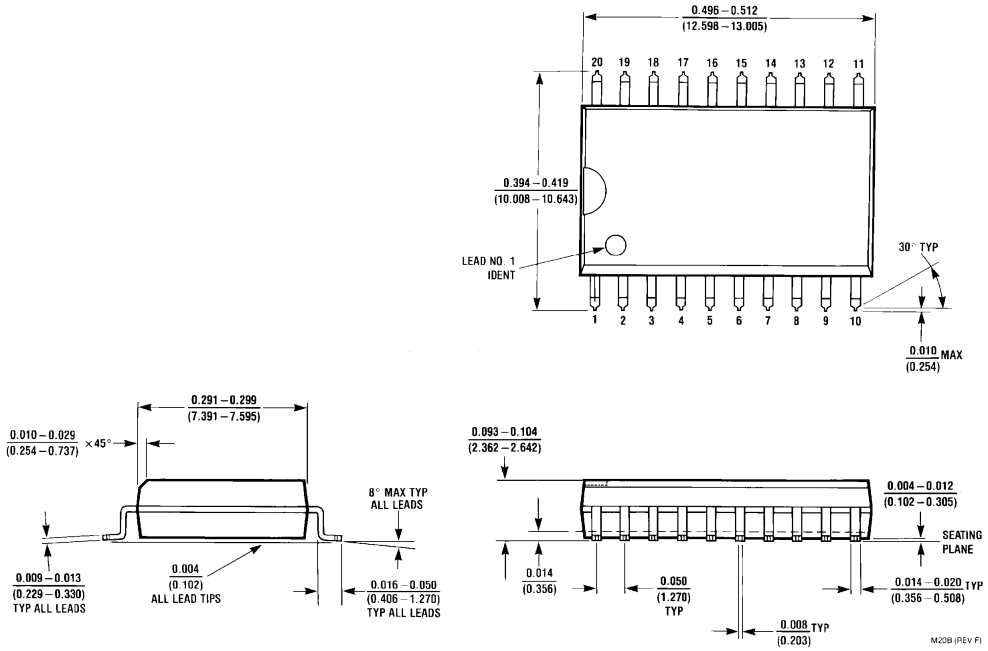
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F).

AC Operating Requirements for VHCT

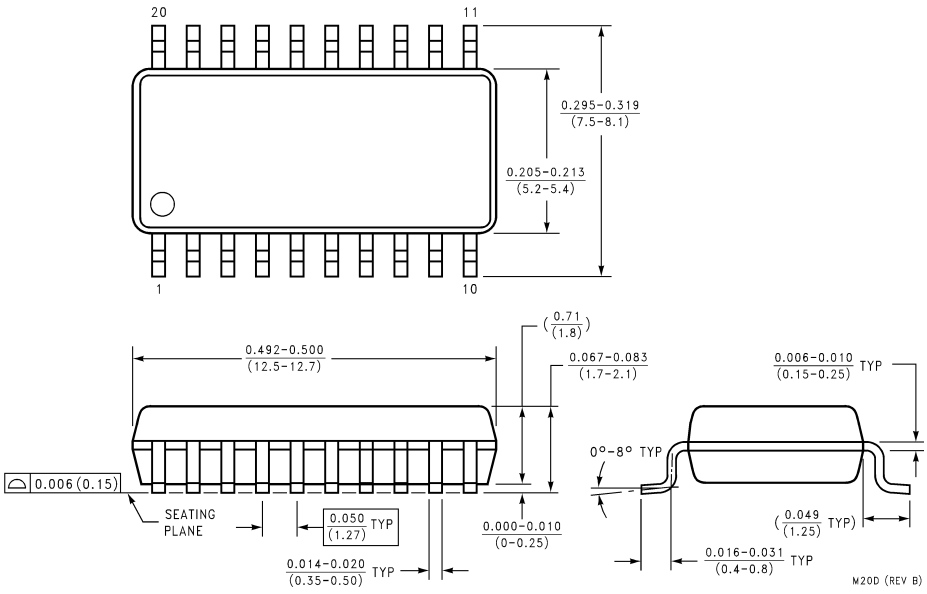
Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units
			Min	Typ	Max	Min	Max	
$t_{W(H)}$	Minimum Pulse Width (CP)	5.0 ± 0.5	6.5			6.5		ns
$t_{W(L)}$								
t_S	Minimum Set-up Time	5.0 ± 0.5	2.5			2.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	2.5			2.5		



Physical Dimensions inches (millimeters) unless otherwise noted

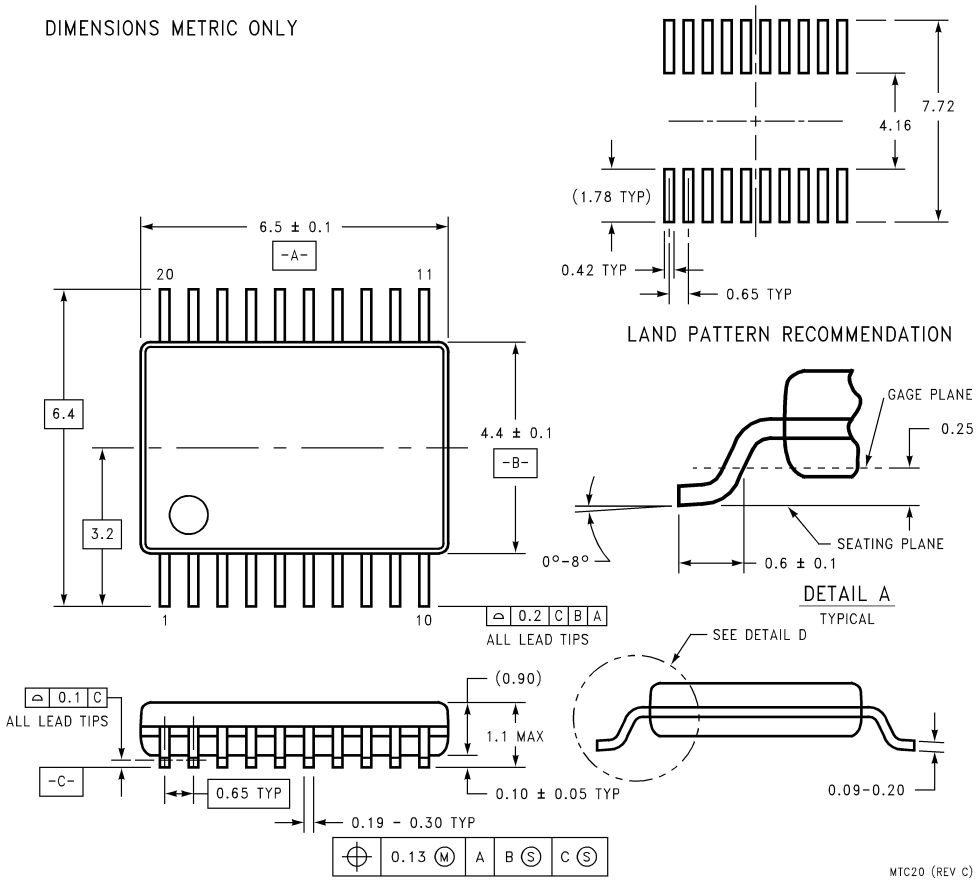


20-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Package Number M20B



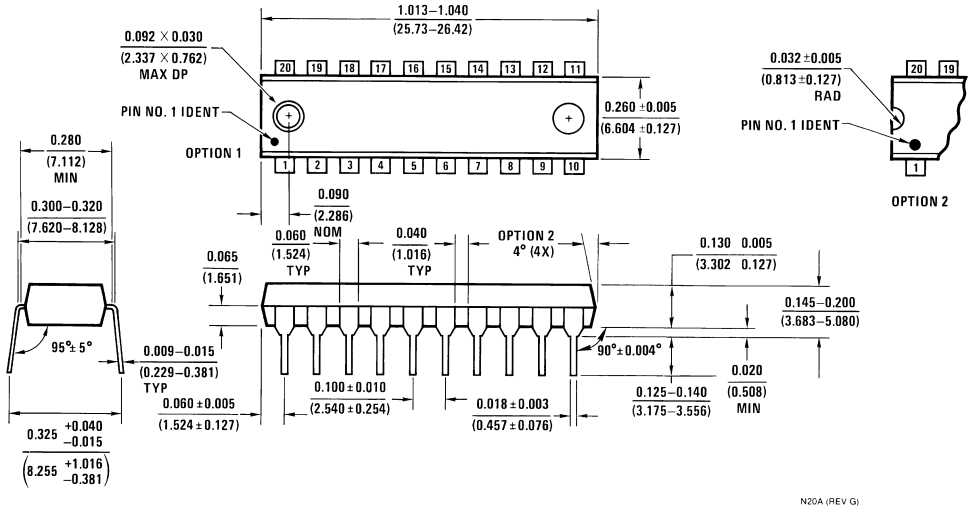
20-Lead Plastic EIAJ SOIC (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic JEDEC TSSOP Type 1 (MTC)
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.300" Wide) Molded Dual-In-Line Package
Package Number N20A

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FAIRCHILD SEMICONDUCTOR™

July 1997
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74VHCT374A
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The VHCT374A is an advanced high speed CMOS octal flip-flop with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type flip-flop is controlled by a clock input (CP) and an output enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Note 1: Outputs in OFF-State.

Features

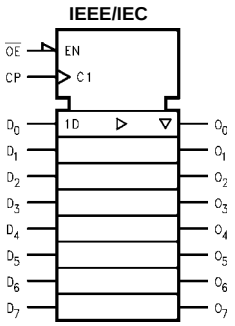
- High speed: f_{MAX} = 140 MHz (typ) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low power dissipation:
  I_{CC} = 4 µA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT374

Ordering Code:

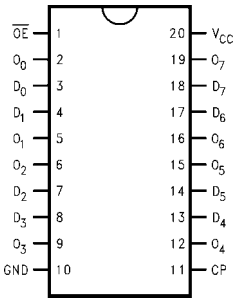
Order Number	Package Number	Package Description
74VHCT374AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT374ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT374AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT374AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input 3-STATE
$\overline{OE}$	Output Enable Input 3-STATE
O_0–O_7	Outputs

Functional Description

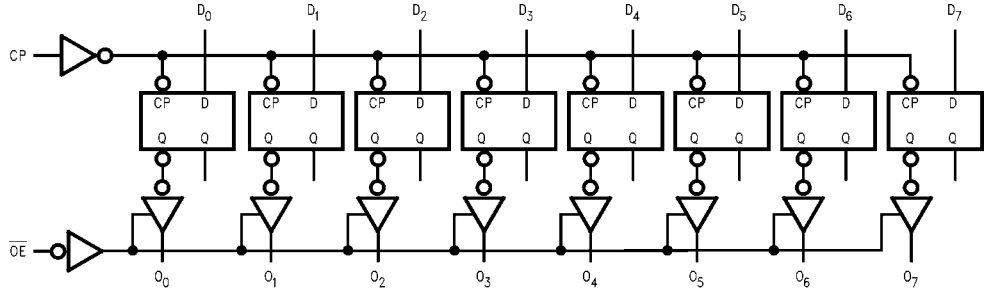
The VHCT374A consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to V_{CC} + 0.5V
(Note 4)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
			3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = +50 uA
					0.36		0.44	V		I_{OL} = +8 mA
I_{OZ}	3-STATE Output OFF-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	µA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	C_L = 50 pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.2	−1.6	V	C_L = 50 pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 7: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time	5.0 ± 0.5		4.1	9.4	1.0	10.5	ns		C_L = 15 pF
t_{PHL}				5.6	10.4	1.0	11.5			C_L = 50 pF
t_{PZL}	3-STATE Output Enable Time	5.0 ± 0.5		6.5	10.2	1.0	11.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}				7.3	11.2	1.0	12.5			C_L = 50 pF
t_{PLZ}	3-STATE Output Disable Time	5.0 ± 0.5		7.0	11.2	1.0	12.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}										
t_{OSLH}	Output to Output Skew	5.0 ± 0.5			1.0		1.0		(Note 8)	
t_{OSHL}										
f_{MAX}	Maximum Clock Frequency	5.0 ± 0.5	90	140		80		MHz		C_L = 15 pF
			85	130		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			25				pF	(Note 9)	

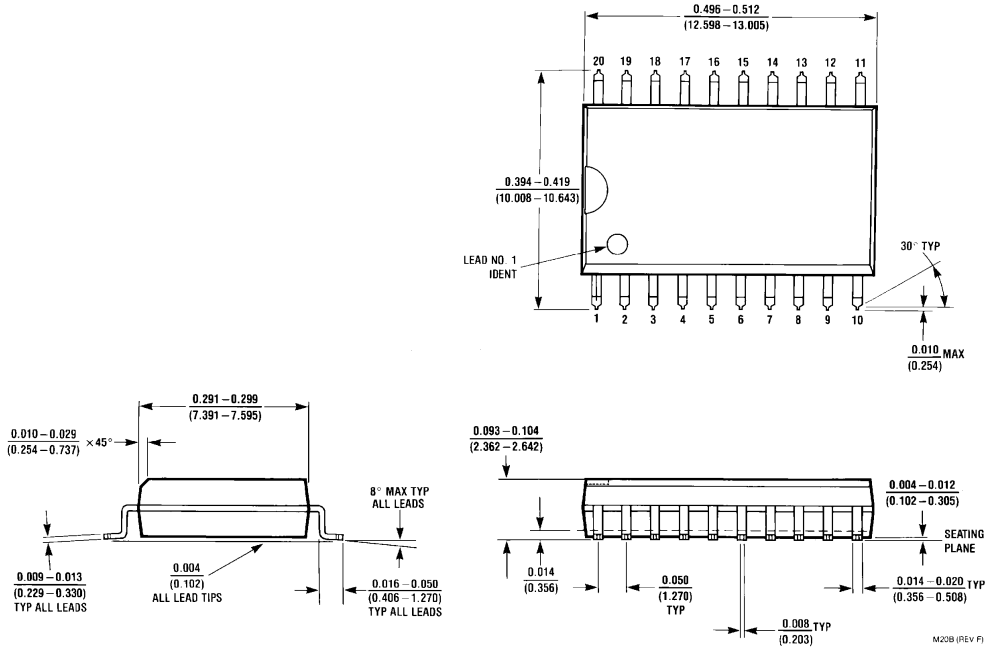
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F). The total C_{PD} when n pcs. of the octal D Flip-Flop operates can be calculated by the equation: C_{PD}(total) = 20 + 12m.

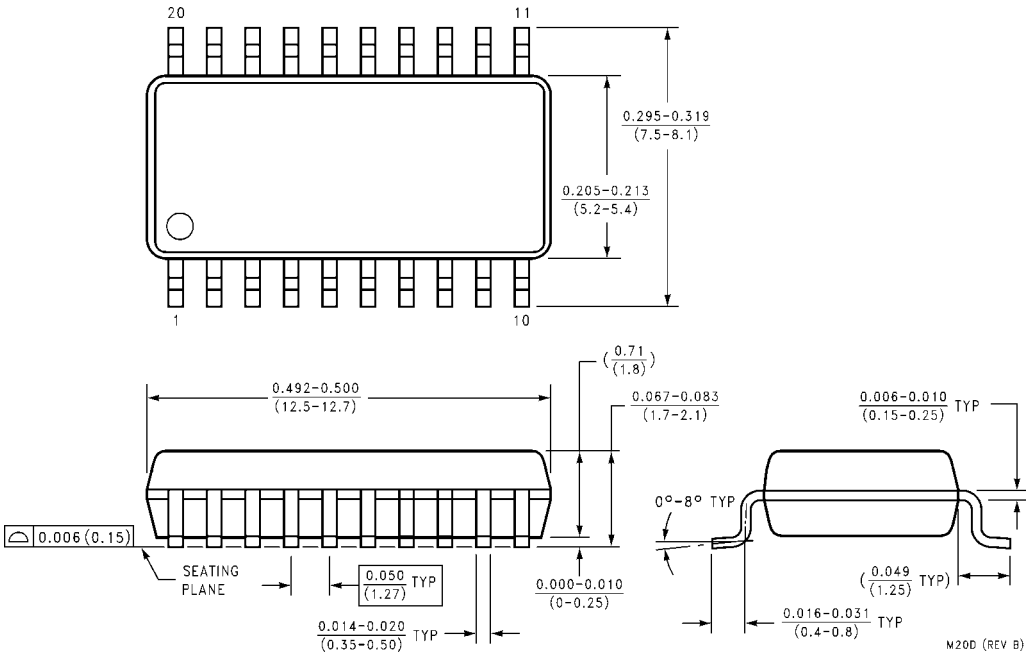
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
t_W(H)	Minimum Pulse Width (CP)	5.0 ± 0.5	6.5			8.5		ns
t_W(L)								
t_S	Minimum Set-up Time	5.0 ± 0.5	2.5			2.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	2.5			2.5		

Physical Dimensions inches (millimeters) unless otherwise noted

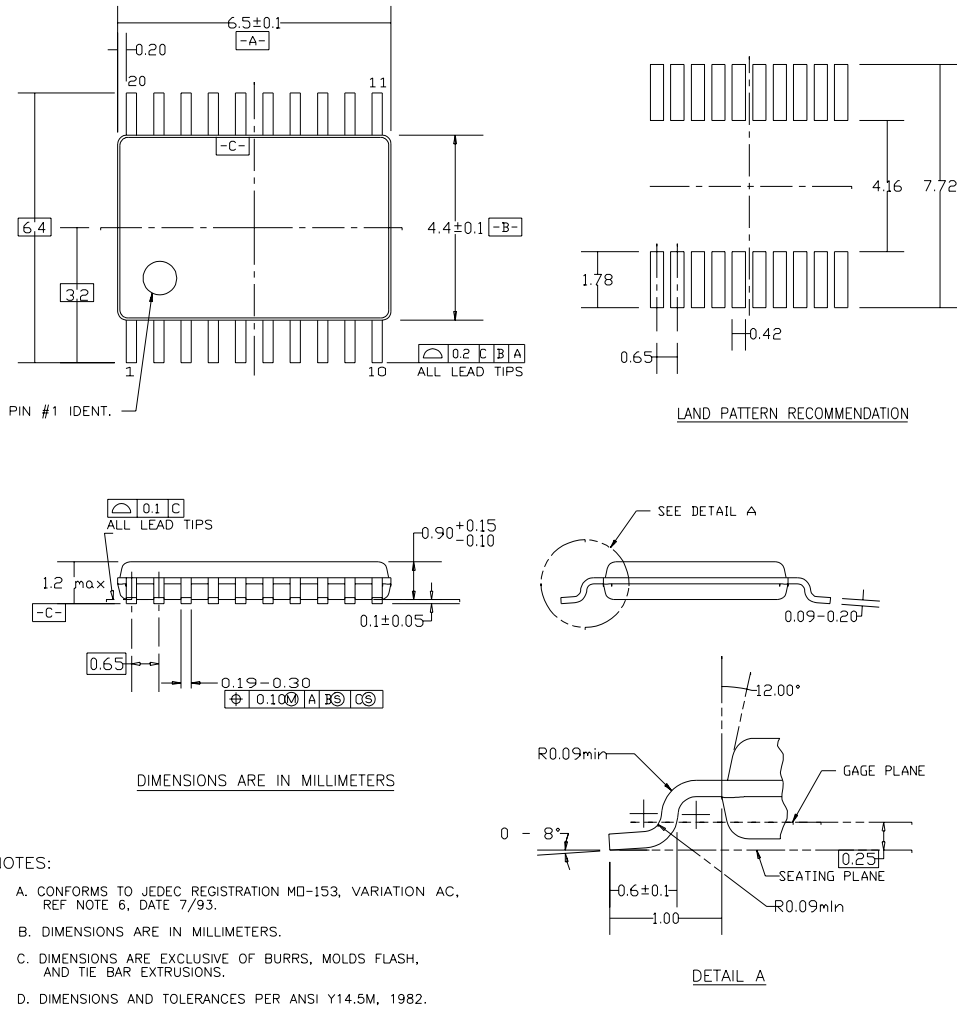


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

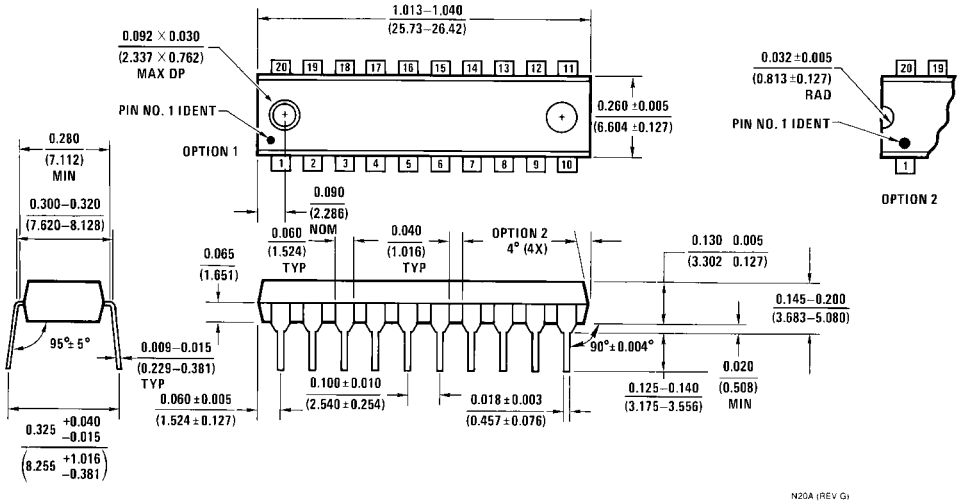
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

June 1997
Revised April 1999

74VHCT540A
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHCT540A is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHCT540A is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

This device is similar in function to the VHCT240A while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Note 1: Outputs in OFF-STATE

Features

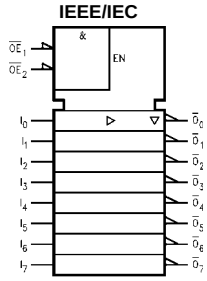
- High Speed: t_{PD} = 5.4 ns (typ) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- Power down protection is provided on all inputs and outputs
- Pin and function compatible with 74HCT540

Ordering Code:

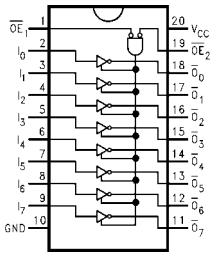
Order Number	Package Number	Package Dissipation
74VHCT540AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT540ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT540AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT540AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0 - I_7	Inputs
$\overline{O}_0$ - $\overline{O}_7$	3-STATE Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	L
H	X	X	Z
X	H	X	Z
L	L	L	H

H = HIGH Voltage Level X = Immaterial
L = LOW Voltage Level Z = High Impedance

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to +7.0V
(Note 4)	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 4)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ≈ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: When outputs are in OFF-STATE or when V_{CC} = OV.

Note 4: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 5: V_{OUT} <GND, V_{OUT} > $V_{CC\ (outputs\ active)}$.

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5 – 5.5	2.0			2.0		V		
V_{IL}	LOW Level Input Voltage	4.5 – 5.5			0.8		0.8	V		
V_{OH}	HIGH Level	4.5	4.4	4.5		4.4		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
	Output Voltage	4.5	3.94			3.80		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	LOW Level	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
	Output Voltage	4.5			0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{OZ}	3-STATE Output OFF-STATE Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum $I_{CC/input}$	5.5			1.35		1.50	mA	V_{IN} = 3.4V other inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current	0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	C_L = 50 pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.2	1.6	V	C_L = 50 pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 7)	Maximum HIGH Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 7: Parameter guaranteed by design.

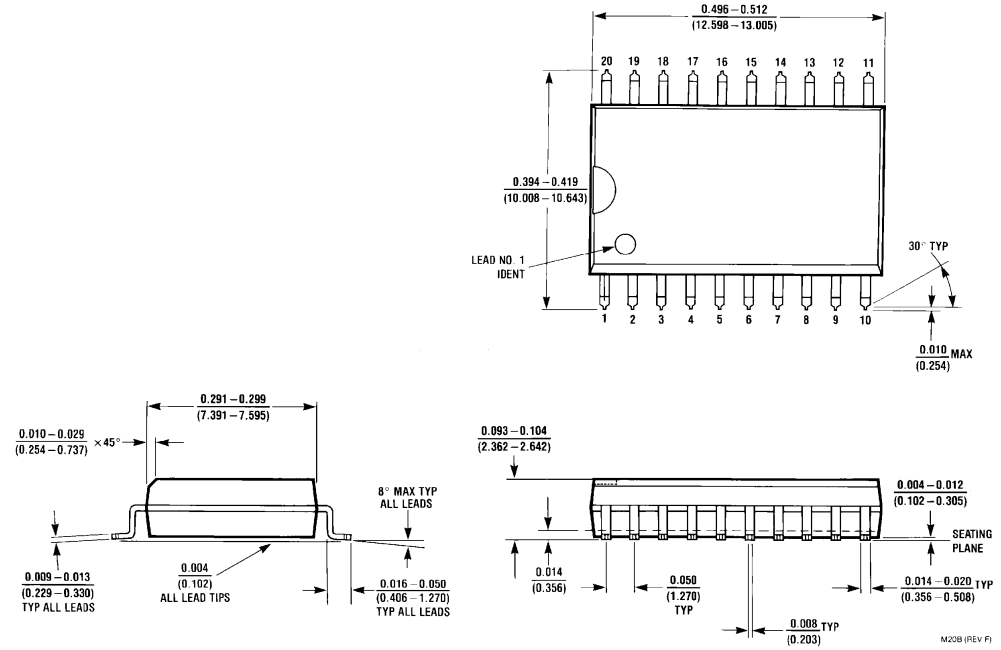
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ± 0.5		5.4	7.4	1.0	8.5	ns		$C_L = 15$ pF
t_{PHL}	Time			5.9	8.4	1.0	9.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		8.3	11.3	1.0	13.0	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			8.8	12.3	1.0	14.0			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		9.4	11.9	1.0	13.5	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to Output	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	$C_L = 50$ pF
t_{OSHL}	Skew									
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 9)	

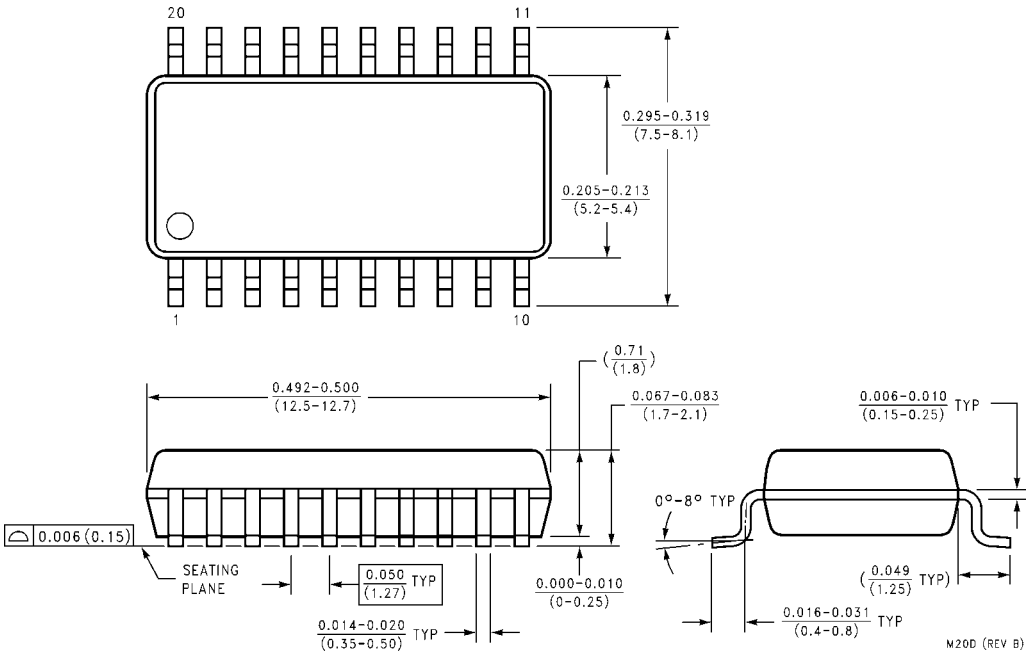
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSLH} = |t_{PHLmax} - t_{PHLmin}|$.

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

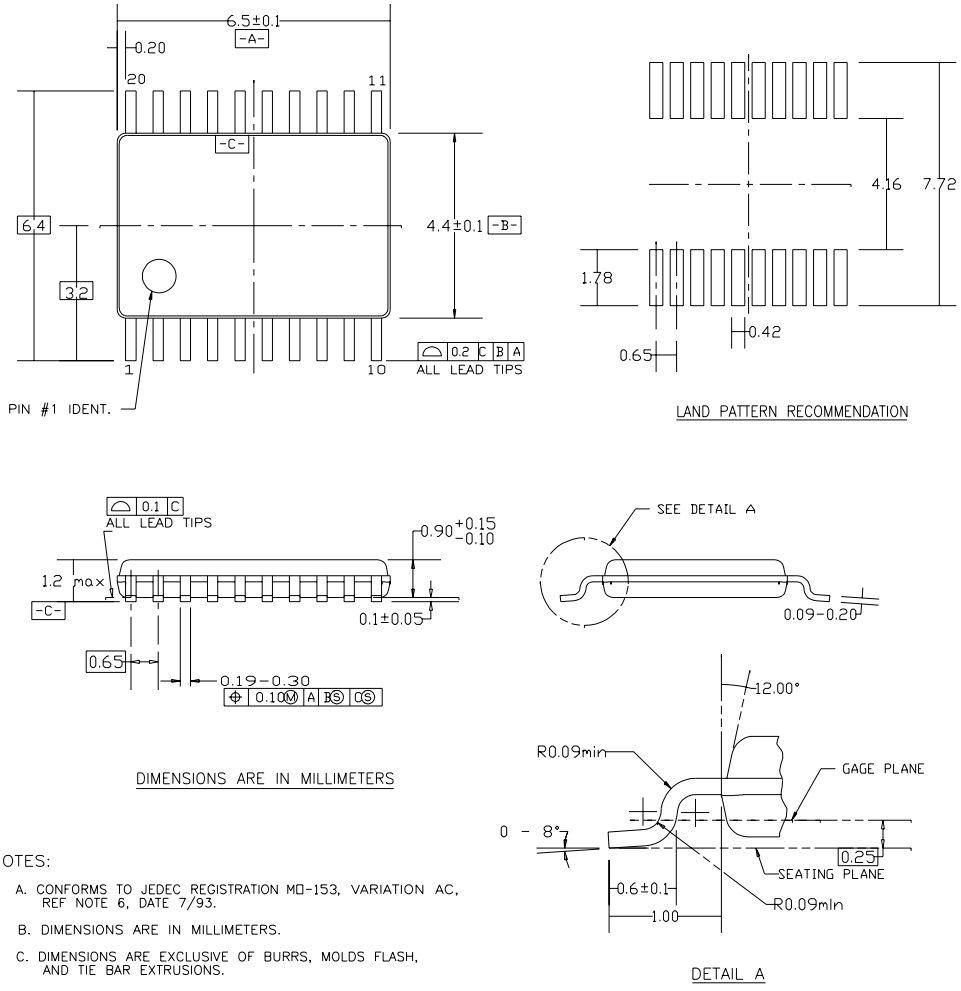


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

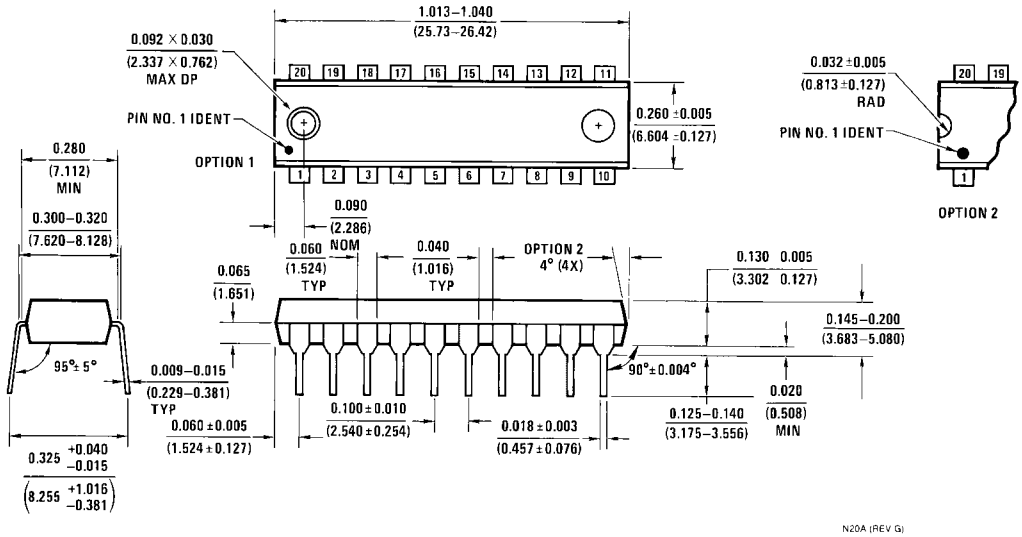
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

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FAIRCHILD SEMICONDUCTOR™

June 1997
Revised April 1999

74VHCT541A
Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHCT541A is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHCT541A is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

This device is similar in function to the VHCT244A while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Note 1: Outputs in OFF-state.

Features

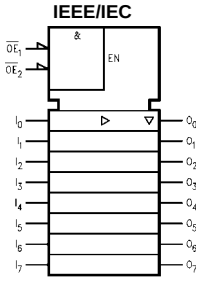
- High Speed: t_{PD} = 5.5 ns (typ) at V_{CC} = 5V
- Low power dissipation: I_{CC} = 4 μA (max) at T_A = 25°C
- Power down protection is provided on all inputs and outputs
- Pin and function compatible with 74HCT541

Ordering Code:

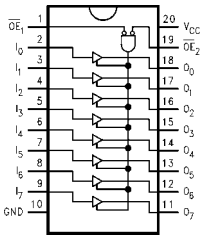
Order Number	Package Number	Package Description
74VHCT541AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT541ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT541AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT541AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0 - I_7	Inputs
O_0 - O_7	3-STATE Outputs

Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level X = Immaterial L = LOW Voltage Level
Z = High Impedance

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to 7.0V
(Note 4)	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 4)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: When Outputs are in OFF-State OR when V_{CC} = 0V.

Note 4: HIGH or LOW state I_{OUT} absolute maximum rating must be observed.

Note 5: V_{OUT} <GND,.V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5 – 5.5	2.0			2.0		V		
V_{IL}	LOW Level Input Voltage	4.5 – 5.5			0.8		0.8	V		
V_{OH}	HIGH Level Output Voltage	4.5	4.4	4.5		4.4		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
		4.5	3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IL}	I_{OL} = +50 μA
		4.5			0.36		0.44	V		I_{OL} = +8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V; Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current	0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	$C_L = 50$ pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.2	−1.6	V	$C_L = 50$ pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	$C_L = 50$ pF
V_{ILD} (Note 7)	Maximum HIGH Level Dynamic Input Voltage	5.0		0.8	V	$C_L = 50$ pF

Note 7: Parameter guaranteed by design.

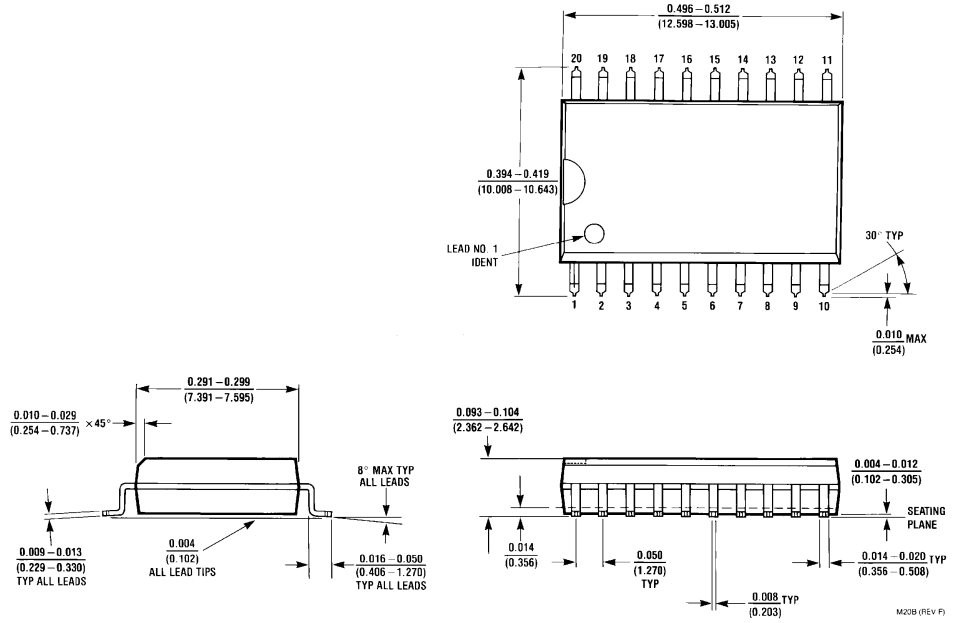
AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ± 0.5		5.0	6.9	1.0	8.0	ns		$C_L = 15$ pF
t_{PHL}	Time			5.5	7.9	1.0	9.0			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		8.3	11.3	1.0	13.0	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			8.8	12.3	1.0	14.0			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		9.4	11.9	1.0	13.5	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to Output Skew	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	$C_L = 50$ pF
t_{OSHL}										
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation Capacitance			19				pF	(Note 9)	

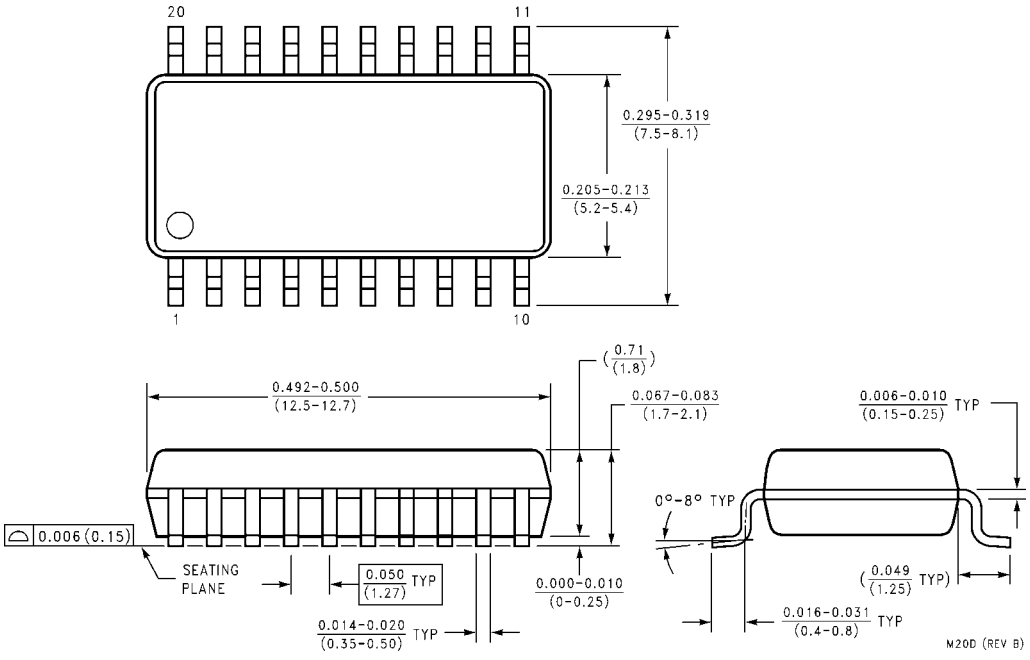
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|$; $t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|$.

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (OPR.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per bit).

Physical Dimensions inches (millimeters) unless otherwise noted

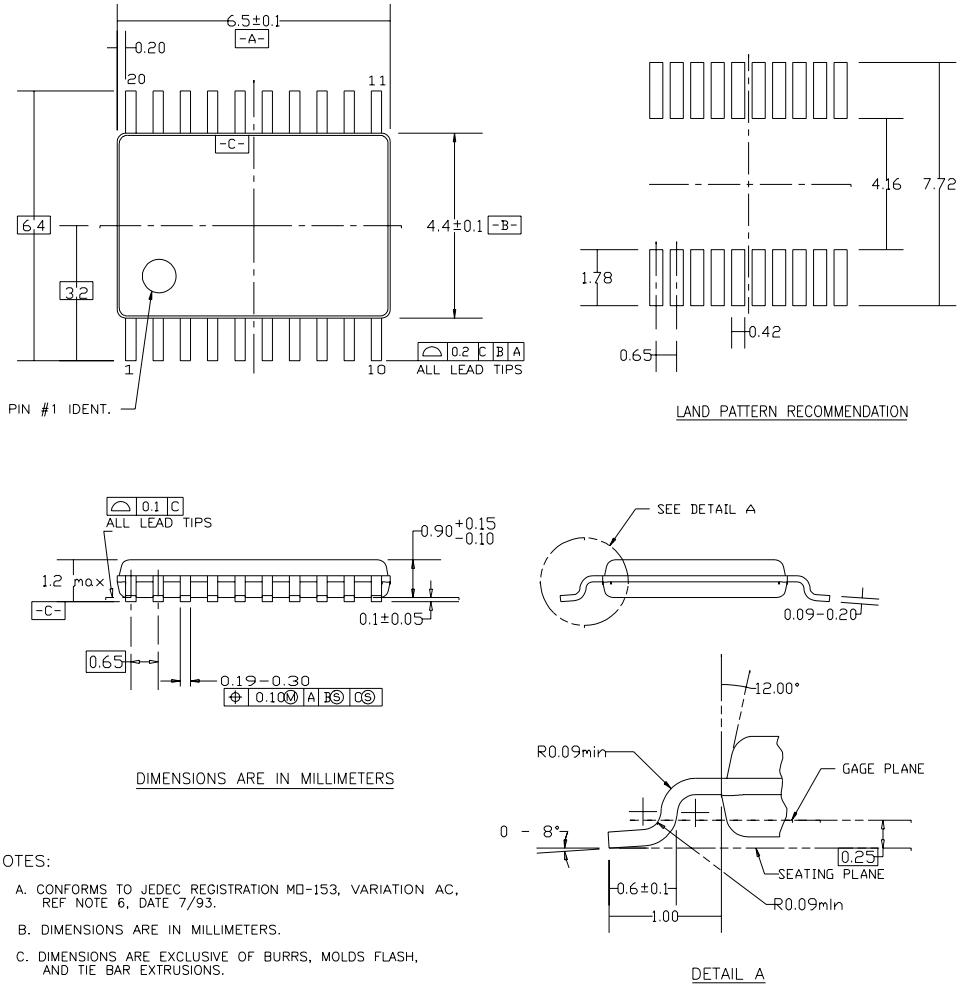


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

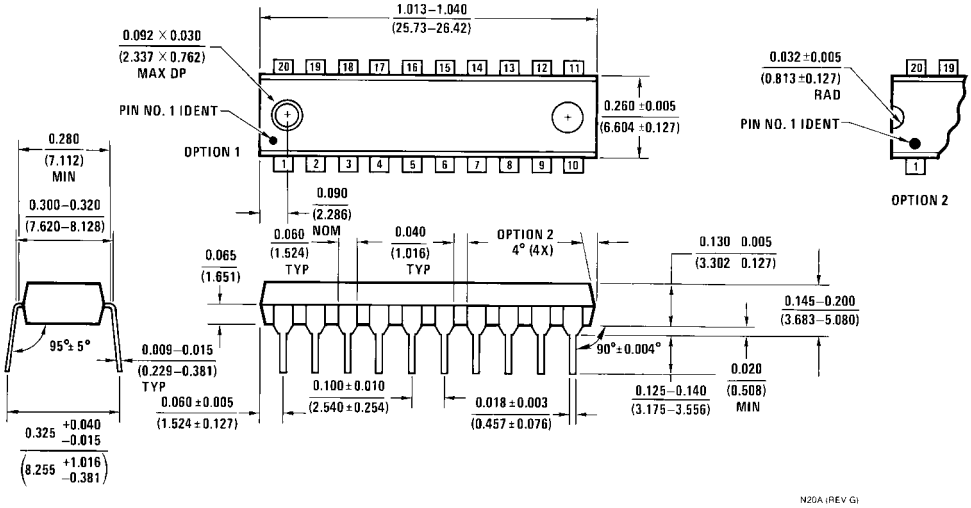
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1998

74VHC573• 74VHCT573
Octal D-Type Latch with 3-STATE Outputs

General Description

The VHC/VHCT573 is an advanced high speed CMOS octal latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a latch enable input (LE) and an Output Enable input ($\overline{OE}$). When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V–7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC : t_{PD} = 5.0 ns (typ) at V_{CC} = 5 V
  VHCT: t_{pd} = 7.7 ns (typ) at V_{CC} = 5V
- High Noise Immunity:
  VHC : $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
  VHCT: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection:
  VHC = inputs only
  VHCT = inputs and outputs
- Low Noise:
  VHC : V_{OLP} = 0.6V (typ)
  VHCT: V_{OLP} = 0.8V (typ)
- Low Power Dissipation:
  I_{CC} = 4 µA (Max) @ T_A = 25˚C
- Pin and function compatible with 74HC/HCT573

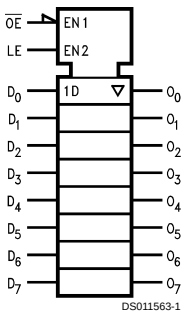
Ordering Code:

Commercial	Package Number	Package Description
74VHC573M	M20B	20-Lead Molded JEDEC SOIC
74VHC573SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC573MTC	MTC20	20-Lead Molded JEDEC Type I TSSOP
74VHC573N	N20A	20-Lead Molded DIP
74VHCT573M	M20B	20-Lead Molded JEDEC SOIC
74VHCT573SJ	M20D	20-Lead Molded EIAJ SOIC
74VHCT573MTC	MTC20	20-Lead Molded JEDEC Type I TSSOP
74VHCT573N	N20A	20-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

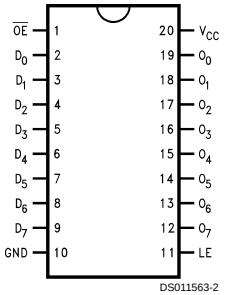
IEEE/IEC



DS011563-1

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



DS011563-2

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Table

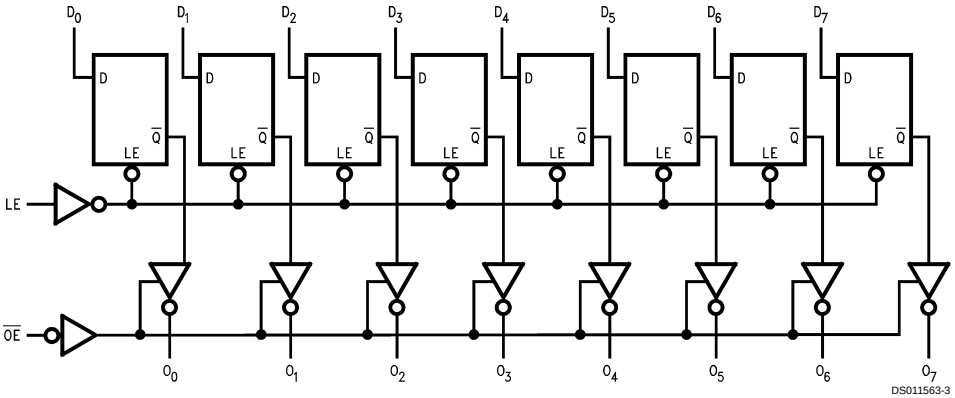
Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Functional Description

The VHC/VHCT573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs, a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode, but, this does not interfere with entering new data into the latches.

Logic Diagram



DS011563-3

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} +0.5V
VHCT*	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260˚C

*V_{OUT}> V_{CC} only if output is in H or Z state

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	
VHC	2.0V to +5.5V
VHCT	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	
VHC/VHCT	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input	2.0	1.50			1.50		V		
	Voltage	3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input	2.0			0.50		0.50	V		
	Voltage	3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH}	
	Voltage	3.0	2.9	3.0		2.9			or V_{IL}	I_{OH} = −50 µA
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH}	
	Voltage	3.0		0.0	0.1		0.1		or V_{IL}	I_{OL} = 50 µA
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}	
	Off-State Current								V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.9	1.2	V	C_L = 50 pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.0	V	C_L = 50 pF
V_{IHD} (Note 3)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 3)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 3: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		4.5	2.5			2.4		V		I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = −50 μA
		4.5			0.36		0.44	V		I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V; Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			±0.5		±0.5	μA	V_{OUT} = 5.5V	

Noise Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.1	1.5	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.0	−1.3	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ±0.3		7.6	11.9	1.0	14.0	ns		C_L = 15 pF
t_{PHL}	Time (LE to O_n)			10.1	15.4	1.0	17.5			C_L = 50 pF
		5.0 ±0.5		5.0	7.7	1.0	9.0	ns		C_L = 15 pF
				6.5	9.7	1.0	11.0			C_L = 50 pF
t_{PLH}	Propagation Delay	3.3 ±0.3		7.0	11.0	1.0	13.0	ns		C_L = 15 pF
t_{PHL}	Time ($D–O_n$)			9.5	14.5	1.0	16.5			C_L = 50 pF
		5.0 ±0.5		4.5	6.8	1.0	8.0			C_L = 15 pF
				6.0	8.8	1.0	10.0			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ±0.3		7.3	11.5	1.0	13.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			9.8	15.0	1.0	17.0			C_L = 50 pF
		5.0 ±0.5		5.2	7.7	1.0	9.0	ns		C_L = 15 pF
				6.7	9.7	1.0	11.0			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ±0.3		10.7	14.5	1.0	16.5	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ±0.5		6.7	9.7	1.0	11.0			C_L = 50 pF
t_{OSLH}	Output to Output Skew	3.3 ±0.3			1.5		1.5	ns	(Note 5)	C_L = 50 pF
t_{OSHL}		5.0 ±0.5			1.0		1.0			C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			29				pF	(Note 6)	

Note 5: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per Latch). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 21 + 8n.

AC Operating Requirements for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
$t_{w(H)}$	Minimum Pulse	3.3 ±0.3	5.0			5.0		ns
$t_{w(L)}$	Width (LE)	5.0 ±0.5	5.0			5.0		
t_s	Minimum Setup Time	3.3 ±0.3	3.5			3.5		ns
		5.0 ±0.5	3.5			3.5		
t_h	Minimum Hold Time	3.3 ±0.3	1.5			1.5		ns
		5.0 ±0.5	1.5			1.5		

AC Electrical Characteristics for VHCT

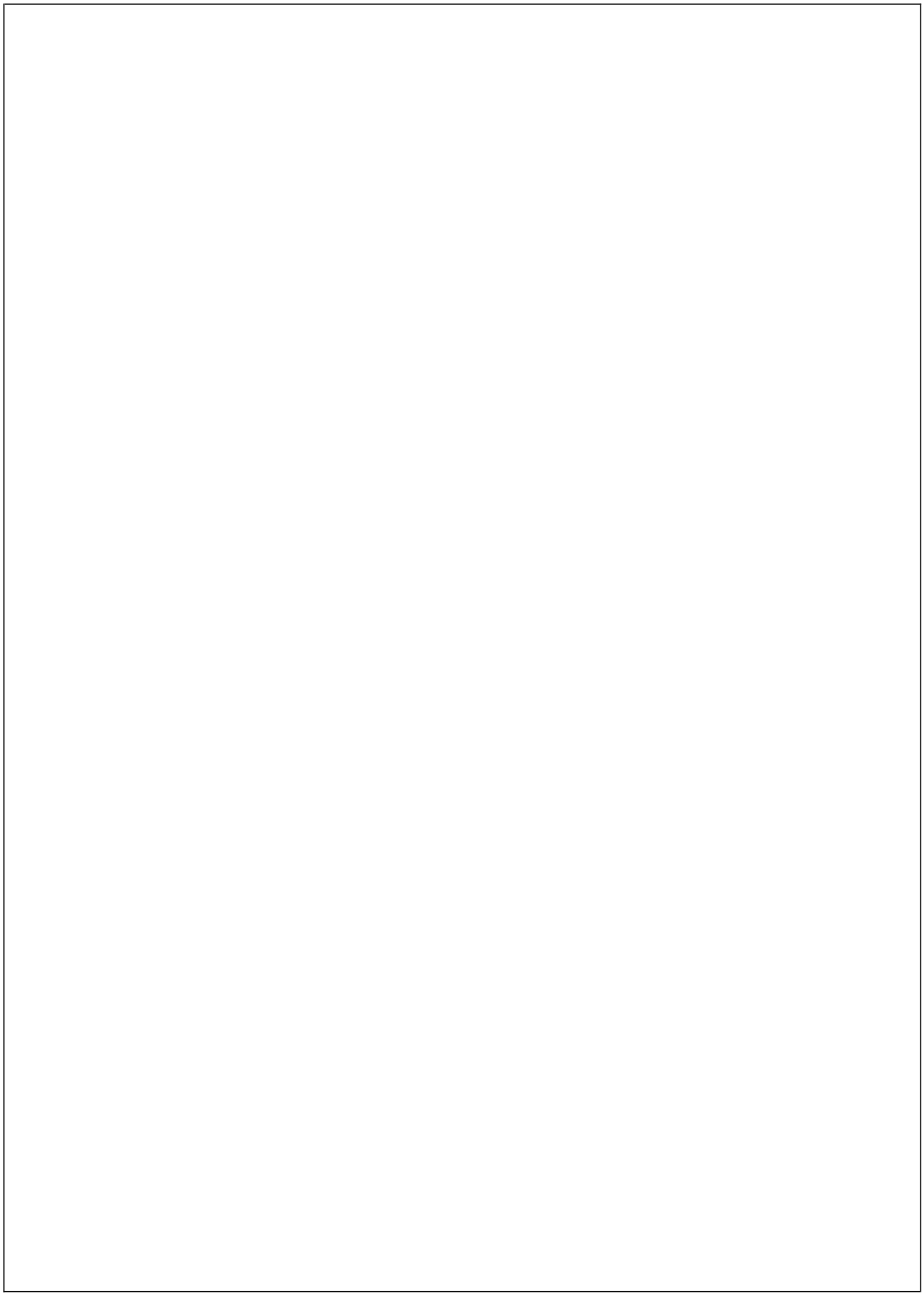
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ±0.5		7.7	12.3	1.0	13.5	ns		C_L = 15 pF
t_{PHL}	Time (LE to O_n)			8.5	13.3	1.0	14.5			C_L = 50 pF
t_{PLH}	Propagation Delay	5.0 ±0.5		5.1	8.5	1.0	9.5	ns		C_L = 15 pF
t_{PHL}	Time (D to O_n)			5.9	9.5	1.0	10.5			C_L = 50 pF
t_{PZL}	3-STATE Output	5.0 ±0.5		6.3	10.9	1.0	12.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			7.1	11.9	1.0	13.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	5.0 ±0.5		6.8	11.2	1.0	12.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to Output	5.0 ±0.5			1.0		1.0	ns	(Note 7)	
t_{OSHL}	Skew									
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation			27				pF	(Note 8)	
	Capacitance									

Note 7: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

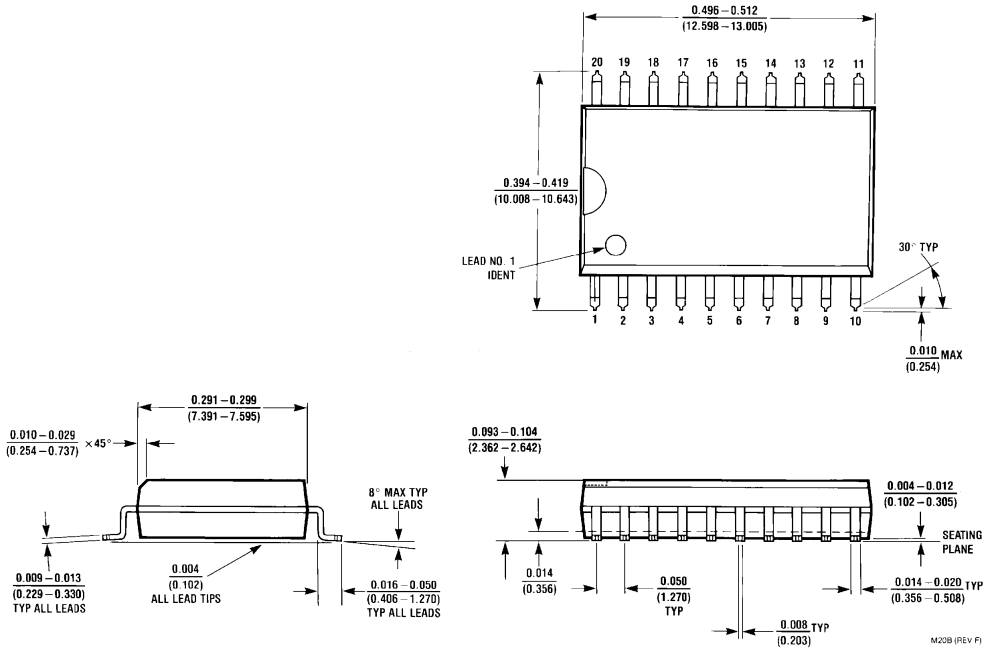
Note 8: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 14 + 13n.

AC Operating Requirements for VHCT

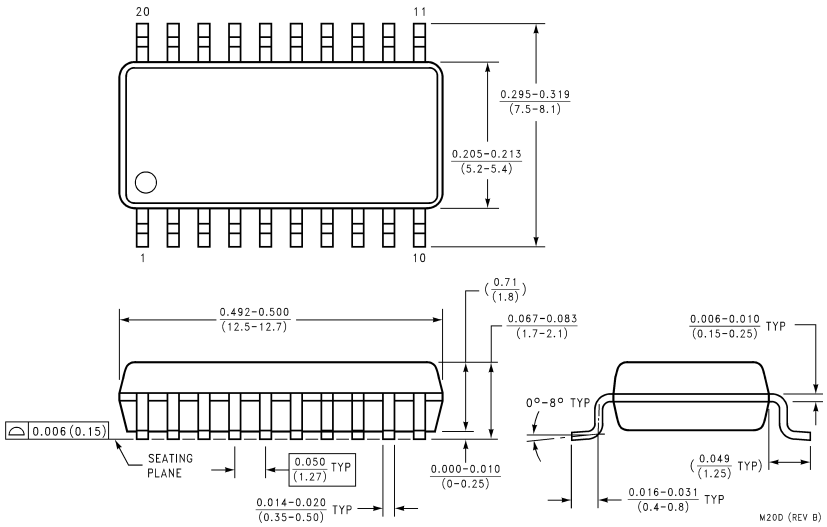
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
$t_{w(H)}$	Minimum Pulse Width (LE)	5.0 ±0.5	6.5			6.5		ns
t_s	Minimum Setup Time	5.0 ±0.5	1.5			1.5		ns
t_h	Minimum Hold Time	5.0 ±0.5	3.5			3.5		ns



Physical Dimensions inches (millimeters) unless otherwise noted

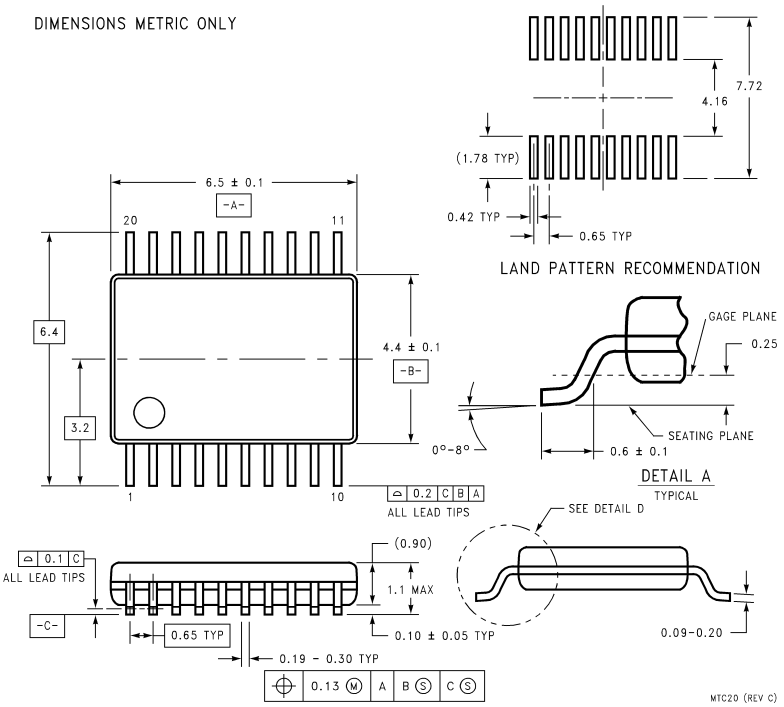


20-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Package Number M20B

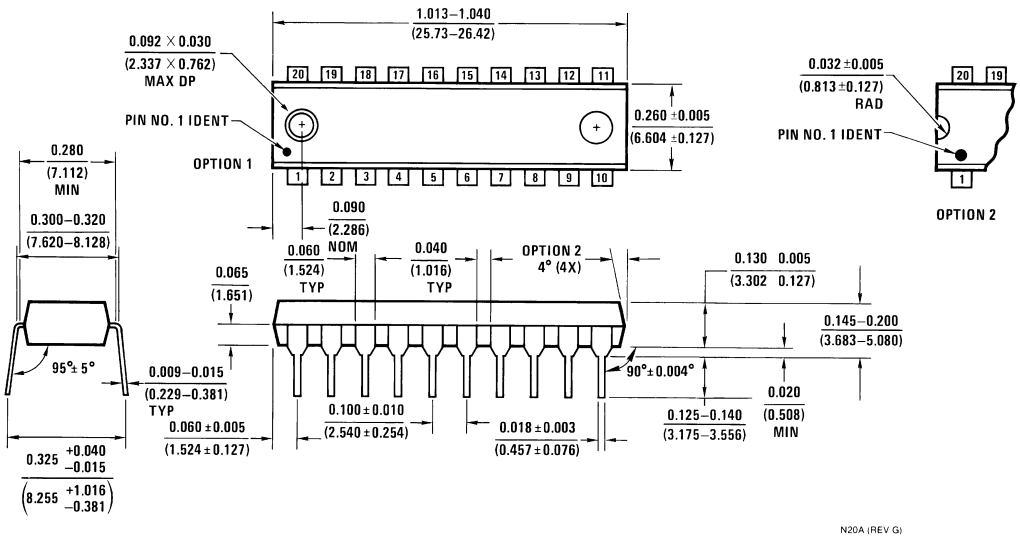


20-Lead Plastic EIAJ SOIC (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Molded Thin Shrink Small Outline Package, JEDEC
Package Number MTC20



20-Lead (0.300" Wide) Molded Dual-In-Line Package
Package Number N20A

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January 1998
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74VHCT573A
Octal D-Type Latch with 3-STATE Outputs

General Description

The VHCT573A is an advanced high speed CMOS octal latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a Latch Enable input (LE) and an Output Enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Note 1: Outputs in OFF-State.

Features

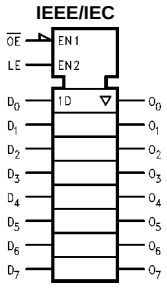
- High speed: t_{PD} = 7.7 ns (typ) at T_A = 25°C
- High Noise Immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection is provided on all inputs and outputs
- Low Noise: V_{OLP} = 1.6V (max)
- Low Power Dissipation:
  I_{CC} = 4 μA (max) @ T_A = 25°C
- Pin and function compatible with 74HCT573

Ordering Code:

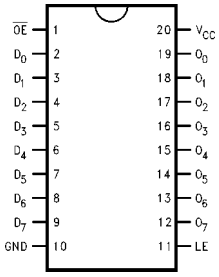
Order Number	Package Number	Package Description
74VHCT573AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT573ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT573AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT573AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Functional Description

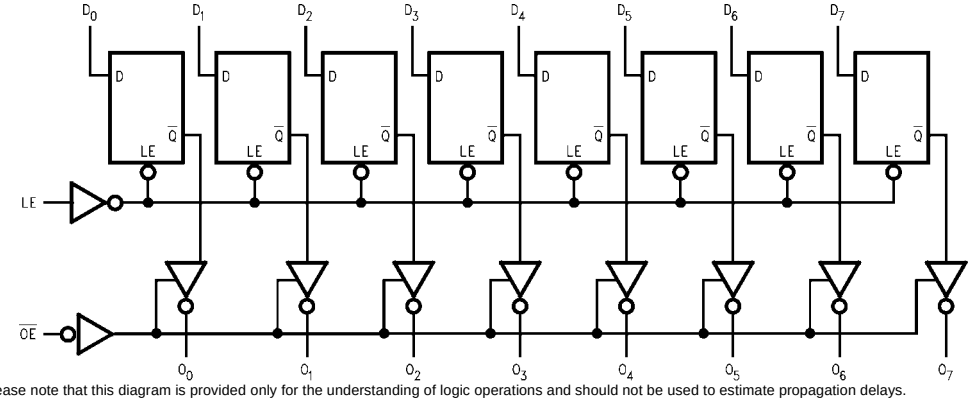
The VHCT573A contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs, a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode, but, this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to V_{CC} + 0.5V
(Note 4)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK}) (Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		4.5	3.94			3.80		V		I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		4.5			0.36		0.44	V		I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V; Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	µA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	C_L = 50 pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.2	−1.6	V	C_L = 50 pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 7: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay Time	5.0 ± 0.5		7.7	12.3	1.0	13.5	ns		$C_L = 15$ pF
t_{PHL}	(LE to O_n)			8.5	13.3	1.0	14.5			$C_L = 50$ pF
t_{PLH}	Propagation Delay Time	5.0 ± 0.5		5.1	8.5	1.0	9.5	ns		$C_L = 15$ pF
t_{PHL}	(D to O_n)			5.9	9.5	1.0	10.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		6.3	10.9	1.0	12.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			7.1	11.9	1.0	13.5			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		8.8	11.2	1.0	12.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to Output	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	
t_{OSHL}	Skew									
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0$V	
C_{PD}	Power Dissipation			25				pF	(Note 9)	
	Capacitance									

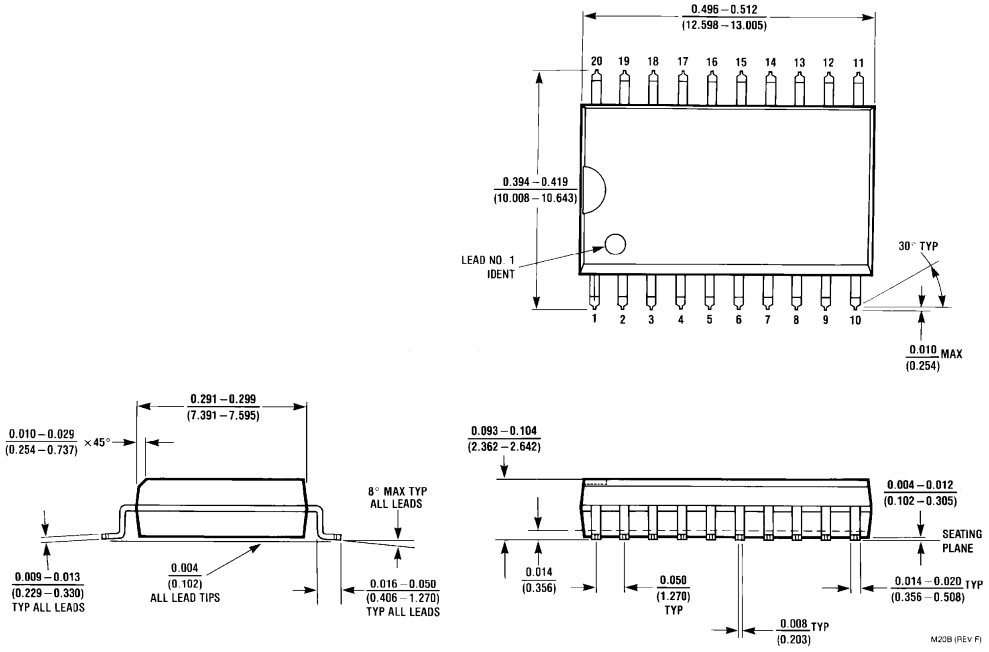
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 14 + 13n.

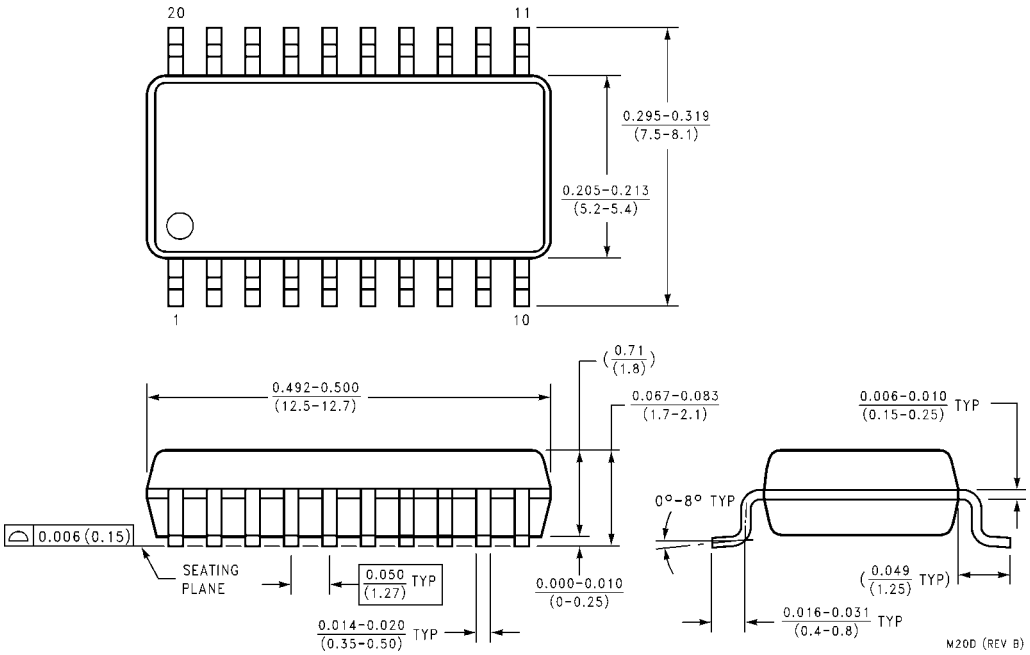
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
t_W(H)	Minimum Pulse Width (LE)	5.0 ± 0.5	6.5			8.5		ns
t_S	Minimum Setup Time	5.0 ± 0.5	1.5			1.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	3.5			3.5		ns

Physical Dimensions inches (millimeters) unless otherwise noted

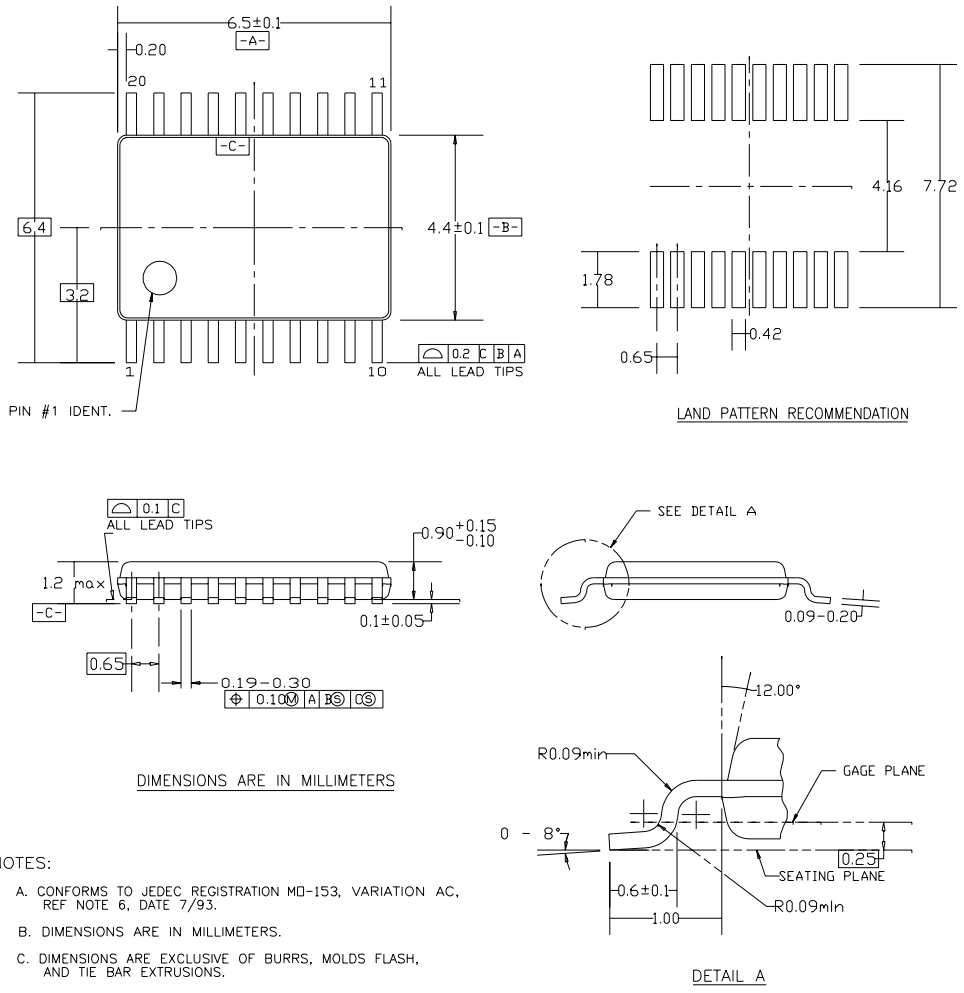


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

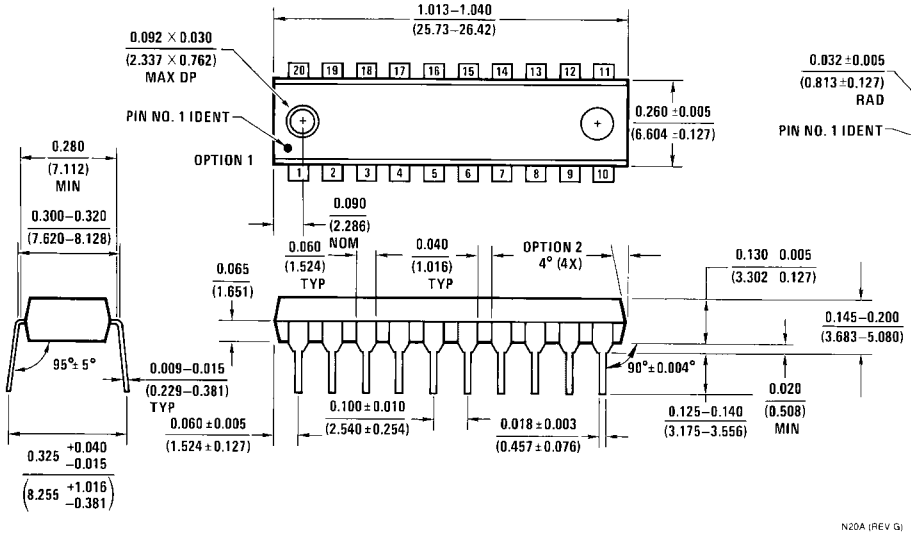
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

February 1998

74VHC574 • 74VHCT574
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The VHC574/VHCT574 is an advanced high speed CMOS octal flip-flop with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type flip-flop is controlled by a clock input (CP) and an output enable input ($\overline{OE}$). When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V–7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC: t_{pd} = 5.6 ns (typ) at V_{CC} = 5 V
  VHCT: t_{pd} = 5.6 ns (typ) at V_{CC} = 5V
- High Noise Immunity:
  VHC: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
  VHCT: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection:
  VHC: Inputs Only
  VHCT: Inputs and Outputs
- Low Noise:
  VHC: V_{OLP} = 0.6V (typ)
  VHCT: V_{OLP} = 0.8V (typ)
- Low Power Dissipation:
  I_{CC} = 4 µA (Max) @ T_A = 25˚C
- Pin and Function Compatible with 74HC/HCT574

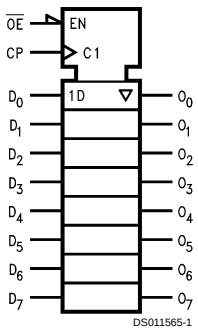
Ordering Code:

Commercial	Package Number	Package Description
74VHC574M	M20B	20-Lead Molded JEDEC SOIC
74VHCT574M	M20B	20-Lead Molded JEDEC SOIC
74VHC574SJ	M20D	20-Lead Molded EIAJ SOIC
74VHCT574SJ	M20D	20-Lead Molded EIAJ SOIC
74VHC574MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHCT574MTC	MTC20	20-Lead Molded JEDEC Type 1 TSSOP
74VHC574N	N20A	20-Lead Molded DIP
74VHCT574N	N20A	20-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

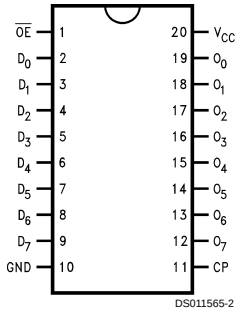
IEEE/IEC



DS011565-1

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



DS011565-2

Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Truth Tables

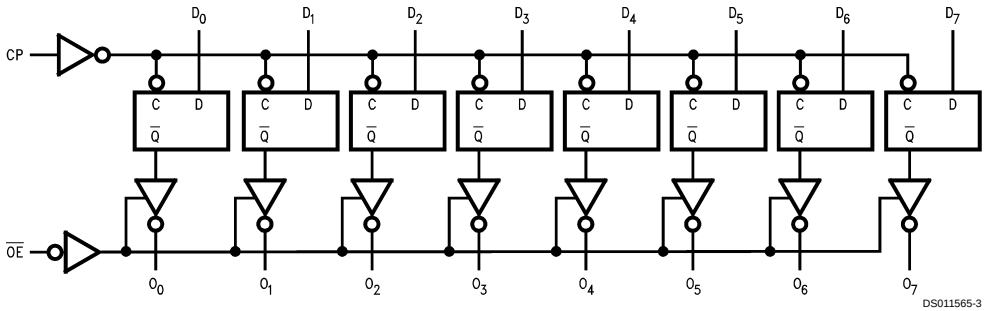
Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Functional Description

The VHC/VHCT574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Logic Diagram



DS011565-3

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 1)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current	
(VHC)	±20 mA
(VHCT)	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260˚C

Recommended Operating Conditions

(Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to +5.5V
VHCT	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	
VHC/VHCT	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: V_{OUT} > V_{CC} only if output is in H or Z state.

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	µA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 4)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.0	1.2	V	C_L = 50 pF
V_{OLV} (Note 4)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.8	−1.0	V	C_L = 50 pF
V_{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C_L = 50 pF
V_{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C_L = 50 pF

Note 4: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level	4.5	2.0			2.0		V		
	Input Voltage	5.5	2.0			20				
V_{IL}	Low Level	4.5			0.8		0.8	V		
	Input Voltage	5.5			0.8		0.8			
V_{OH}	High Level	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
	Output Voltage		2.5			2.4		V	or V_{IL}	I_{OH} = −8 μA
V_{OL}	Low Level	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
	Output Voltage				0.36		0.44	V	or V_{IL}	I_{OL} = 8 μA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Input = V_{CC} or GND	
I_{OPD}	Output Leakage Current (Power Down State)	0.0			±0.5		+5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 5)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.5	V	C_L = 50 pF
V_{OLV} (Note 5)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.0	−1.3	V	C_L = 50 pF
V_{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage	5.0		2.0	V	C_L = 50 pF
V_{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage	5.0		0.8	V	C_L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	3.3 ±0.3		8.5	13.2	1.0	15.5	ns		C_L = 15 pF
t_{PHL}	Time (CP to O_n)			11.0	16.7	1.0	19.0			C_L = 50 pF
		5.0 ±0.5		5.6	8.6	1.0	10.0	ns		C_L = 15 pF
				7.1	10.6	1.0	12.0			C_L = 50 pF
t_{PZL}	3-STATE Output	3.3 ±0.3		8.2	12.8	1.0	15.0	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			10.7	16.3	1.0	18.5			C_L = 50 pF
		5.0 ±0.5		5.9	9.0	1.0	10.5	ns		C_L = 15 pF
				7.4	11.0	1.0	12.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	3.3 ±0.3		11.0	15.0	1.0	17.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time	5.0 ±0.5		7.1	10.1	1.0	11.5			C_L = 50 pF
t_{OSLH}	Output to	3.3 ±0.3			1.5		1.5	ns	(Note 6)	C_L = 50 pF
t_{OSHL}	Output Skew	5.0 ±0.5			1.0		1.0			C_L = 50 pF
f_{MAX}	Maximum Clock	3.3 ±0.3	80	125		65		MHz		C_L = 15 pF
	Frequency		50	75		45				C_L = 50 pF
		5.0 ±0.5	130	180		110				C_L = 15 pF
			85	115		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			6				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			28				pF	(Note 7)	

Note 6: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 8n.

AC Operating Requirements for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
$t_{W(H)}$	Minimum Pulse Width (CP)	3.3 ±0.3	5.0			5.0		ns
$t_{W(L)}$		5.0 ±0.5	5.0			5.0		
t_S	Minimum Set-Up Time	3.3 ±0.3	3.5			3.5		ns
		5.0 ±0.5	3.5			3.5		
t_h	Minimum Hold Time	3.3 ±0.3	1.5			1.5		
		5.0 ±0.5	1.5			1.5		

AC Electrical Characteristics for VHCT Devices

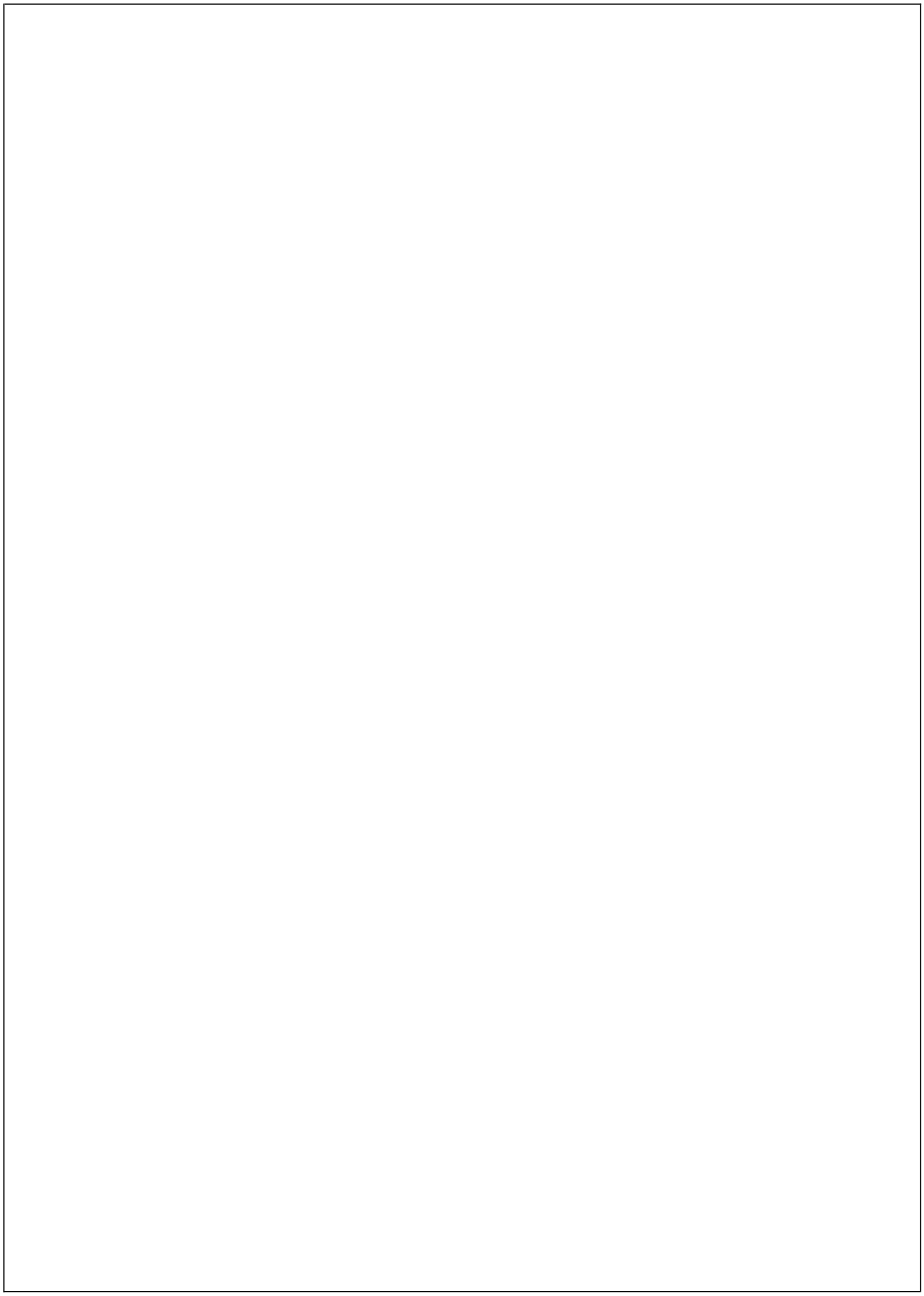
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ±0.5		5.6	9.4	1.0	10.5	ns		C_L = 15 pF
t_{PHL}	Time			6.4	10.4	1.0	11.5			C_L = 50 pF
t_{PZL}	3-STATE Output	5.0 ±0.5		6.5	10.2	1.0	11.5	ns	R_L = 1 kΩ	C_L = 15 pF
t_{PZH}	Enable Time			7.3	11.2	1.0	12.5			C_L = 50 pF
t_{PLZ}	3-STATE Output	5.0 ±0.5		7.0	11.2	1.0	12.0	ns	R_L = 1 kΩ	C_L = 50 pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to	5.0 ±0.5			1.0		1.0	ns	(Note 8)	
t_{OSHL}	Output Skew									
f_{MAX}	Maximum Clock	5.0 ±0.5	90	140		80		MHz		C_L = 15 pF
	Frequency		85	130		75				C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open	
C_{OUT}	Output Capacitance			9				pF	V_{CC} = 5.0V	
C_{PD}	Power Dissipation Capacitance			27				pF	(Note 9)	

Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

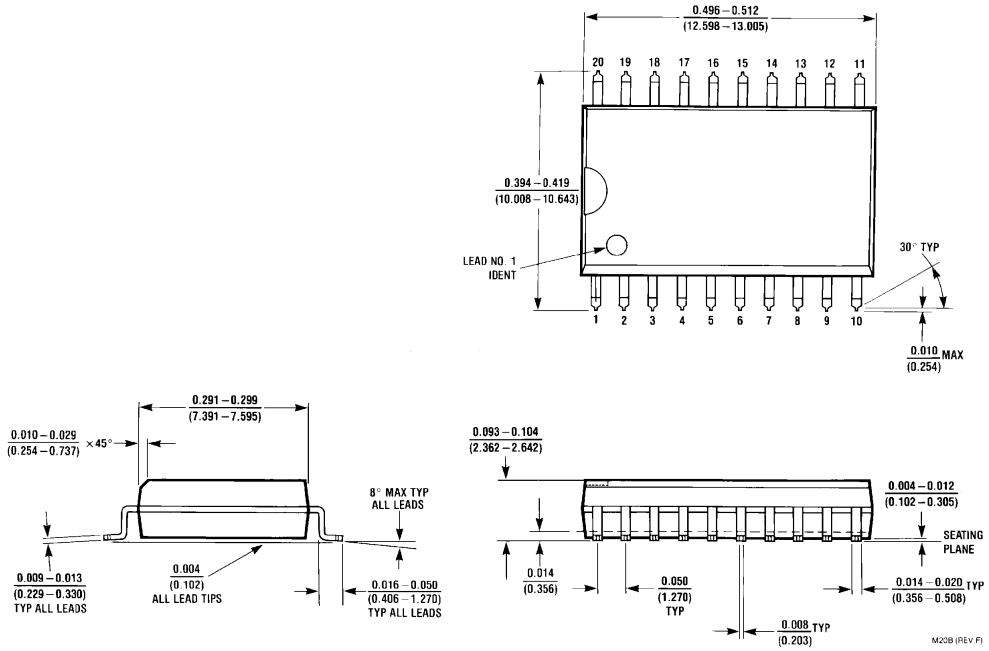
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

AC Operating Requirements for VHCT

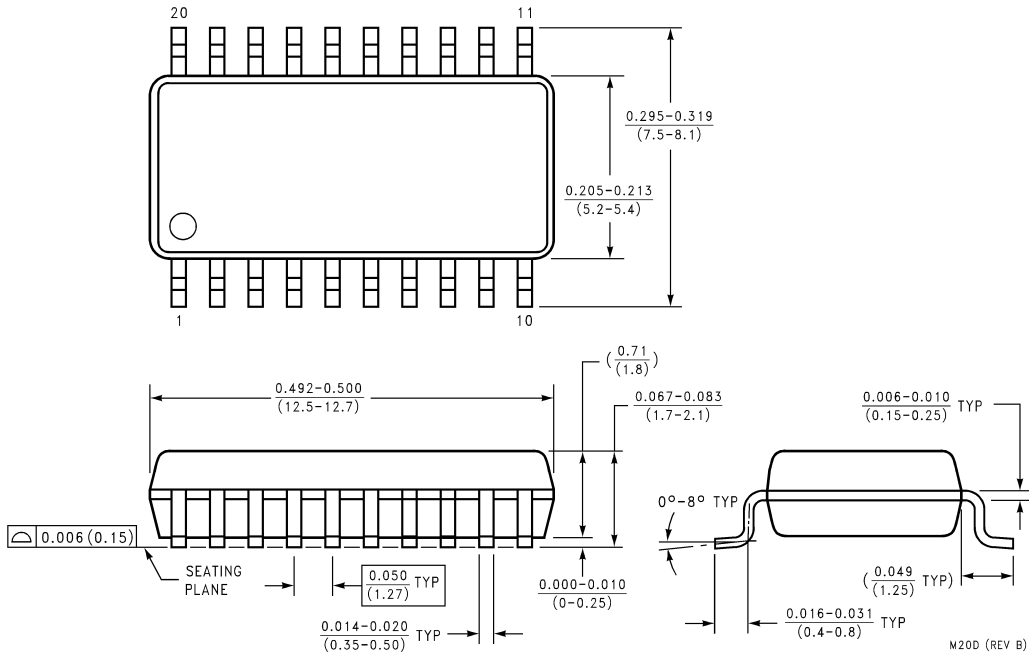
Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units
			Min	Typ	Max	Min	Max	
$t_{W(H)}$	Minimum Pulse Width (CP)	5.0 ±0.5	6.5			6.5		ns
$t_{W(L)}$								
t_S	Minimum Set-Up Time	5.0 ±0.5	2.5			2.5		ns
t_h	Minimum Hold Time	5.0 ±0.5	2.5			2.5		



Physical Dimensions inches (millimeters) unless otherwise noted

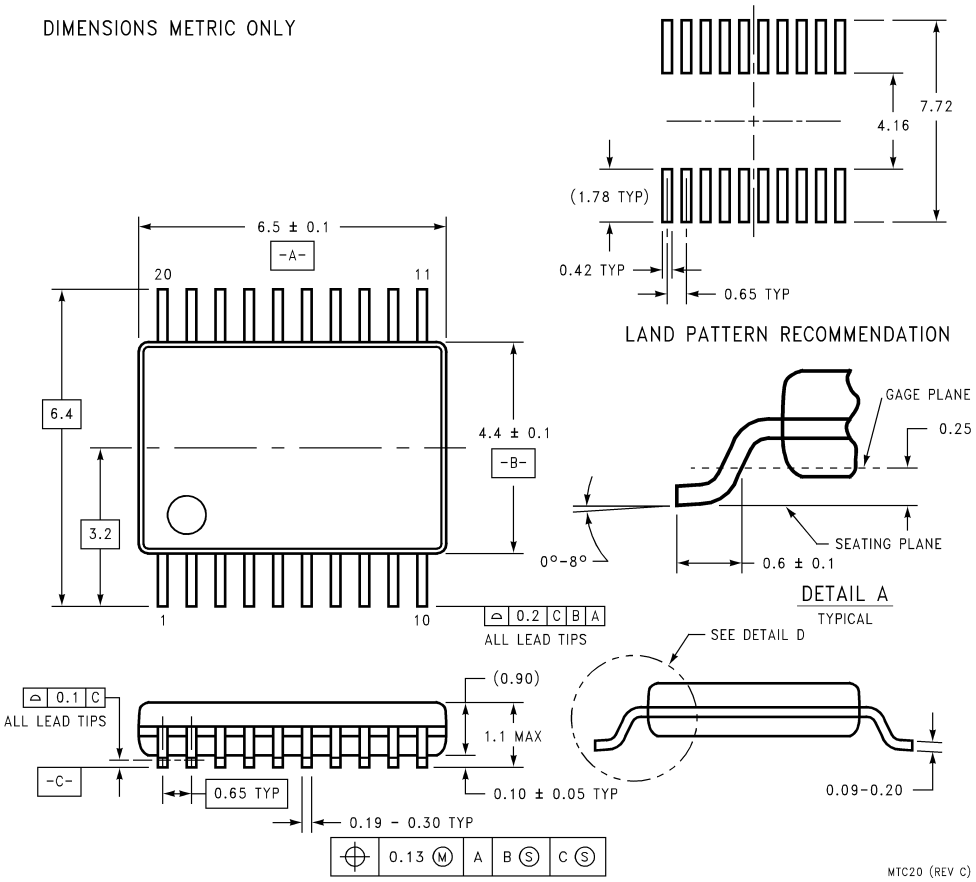


20-Lead Small Outline Integrated Circuit JEDEC SOIC (M)
Package Number M20B



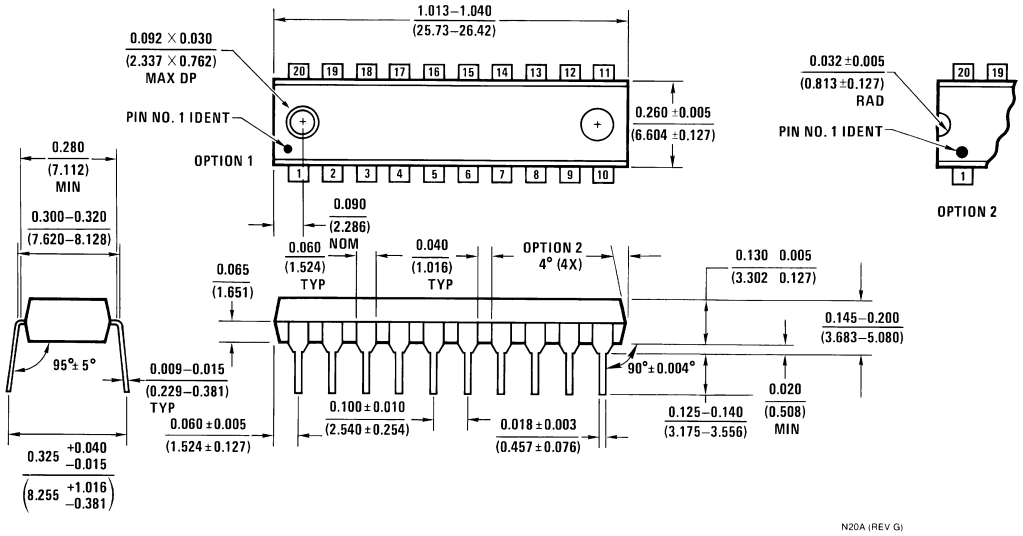
20-Lead Plastic EIAJ SOIC (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Shrink Small Outline JEDEC TSSOP Type 1 (MTC)
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Molded DIP (N)
Package Number N20A

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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FAIRCHILD SEMICONDUCTOR™

July 1997
Revised April 1999

74VHCT574A
Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The VHCT574A is an advanced high speed CMOS octal flip-flop with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type flip-flop is controlled by a clock input (CP) and an Output Enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Note 1: Outputs in OFF-State.

Features

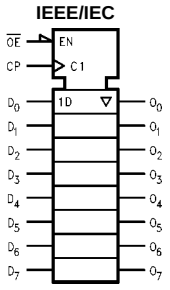
- High speed: f_{MAX} = 140 MHz (typ) at T_A = 25°C
- Power Down Protection is provided on all inputs and outputs.
- Low Noise: V_{OLP} = 1.6V (max)
- Low Power Dissipation:
  I_{CC} = 4 µA (max) @ T_A = 25°C
- Pin and Function Compatible with 74HCT574

Ordering Code:

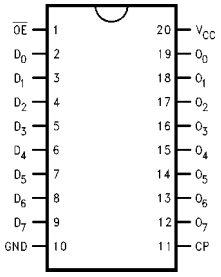
Order Number	Package Number	Package Description
74VHCT574AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT574ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT574AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT574AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
CP	Clock Pulse Input 3-STATE
$\overline{OE}$	Output Enable Input 3-STATE
O_0–O_7	Outputs

Functional Description

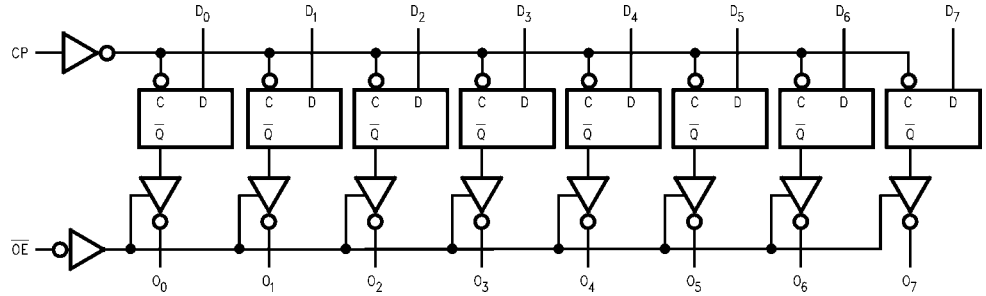
The VHCT574A consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H	⌐	L	H
L	⌐	L	L
X	X	H	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance
⌐ = LOW-to-HIGH Transition

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 3)	−0.5V to V_{CC} + 0.5V
(Note 4)	−0.5V to +7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK}) (Note 5)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC})	4.5V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 3)	0V to V_{CC}
(Note 4)	0V to +5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV.

Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			20				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH}	I_{OH} = −50 μA
			3.94			3.80		V	or V_{IL}	I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH}	I_{OL} = 50 μA
					0.36		0.44	V	or V_{IL}	I_{OL} = 8 mA
I_{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Input = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			0.5		5.0	μA	V_{OUT} = 5.5V	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 7)	Quiet Output Maximum Dynamic V_{OL}	5.0	1.2	1.6	V	$C_L = 50$ pF
V_{OLV} (Note 7)	Quiet Output Minimum Dynamic V_{OL}	5.0	−1.2	−1.6	V	$C_L = 50$ pF
V_{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	$C_L = 50$ pF
V_{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	$C_L = 50$ pF

Note 7: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
t_{PLH}	Propagation Delay	5.0 ± 0.5		4.1	9.4	1.0	10.5	ns		$C_L = 15$ pF
t_{PHL}	Time			5.6	10.4	1.0	11.5			$C_L = 50$ pF
t_{PZL}	3-STATE Output	5.0 ± 0.5		6.5	10.2	1.0	11.5	ns	$R_L = 1$ kΩ	$C_L = 15$ pF
t_{PZH}	Enable Time			7.3	11.2	1.0	12.5			$C_L = 50$ pF
t_{PLZ}	3-STATE Output	5.0 ± 0.5		7.0	11.2	1.0	12.0	ns	$R_L = 1$ kΩ	$C_L = 50$ pF
t_{PHZ}	Disable Time									
t_{OSLH}	Output to	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	
t_{OSHL}	Output Skew									
f_{MAX}	Maximum Clock	5.0 ± 0.5	90	140		80		MHz		$C_L = 15$ pF
	Frequency		85	130		75				$C_L = 50$ pF
C_{IN}	Input			4	10		10	pF	V_{CC} = Open	
	Capacitance									
C_{OUT}	Output			9				pF	$V_{CC} = 5.0V$	
	Capacitance									
C_{PD}	Power Dissipation			25				pF	(Note 9)	
	Capacitance									

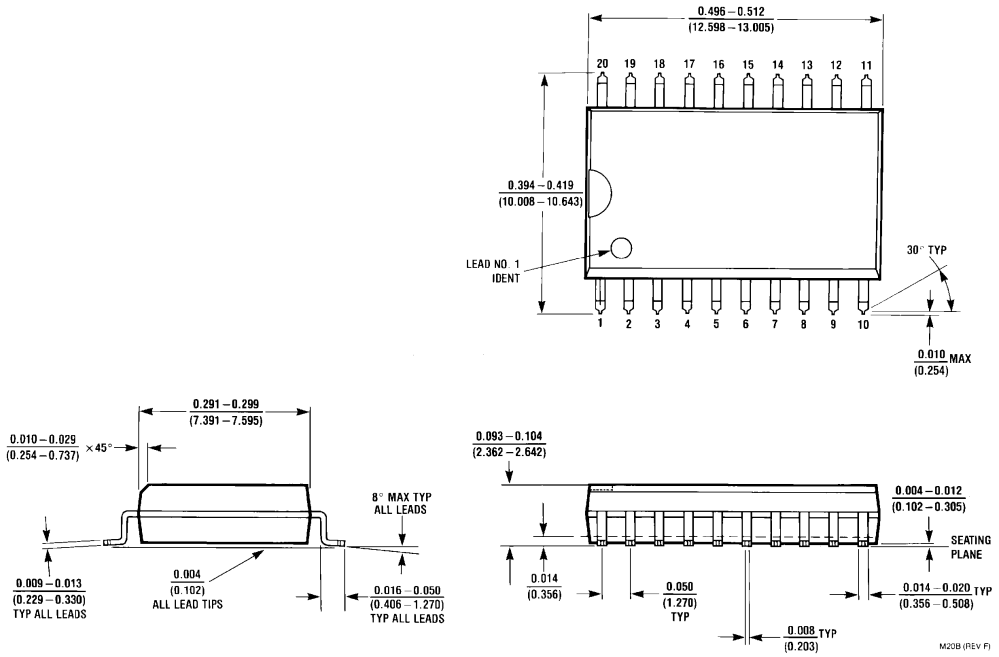
Note 8: Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

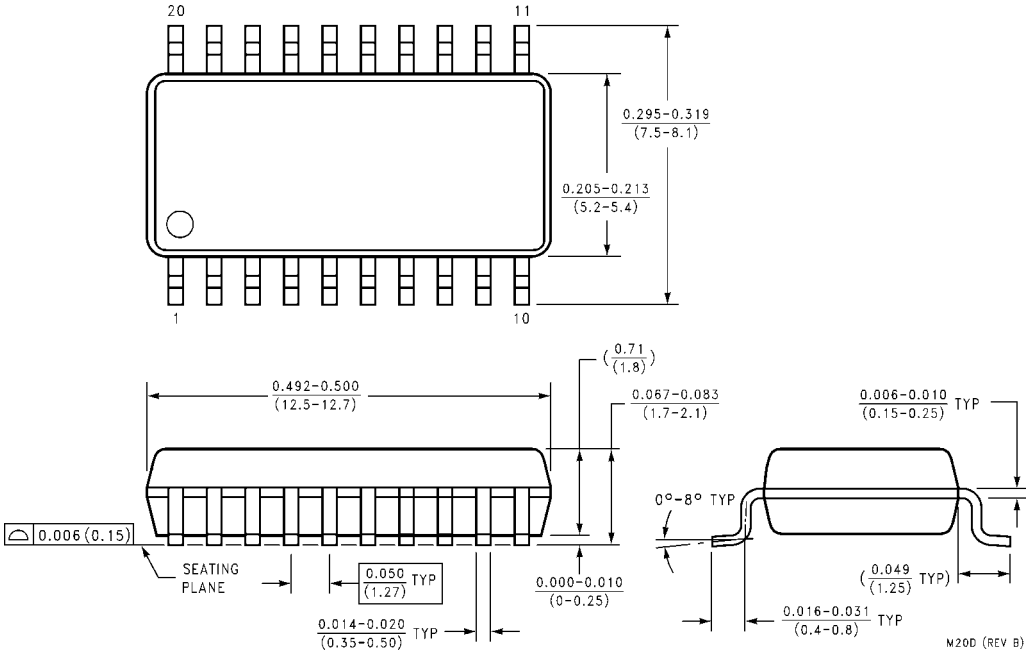
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
			Min	Typ	Max	Min	Max	
$t_W(H)$	Minimum Pulse Width (CP)	5.0 ± 0.5	6.5			8.5		ns
$t_W(L)$								
t_S	Minimum Set-Up Time	5.0 ± 0.5	2.5			2.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	2.5			2.5		

Physical Dimensions inches (millimeters) unless otherwise noted

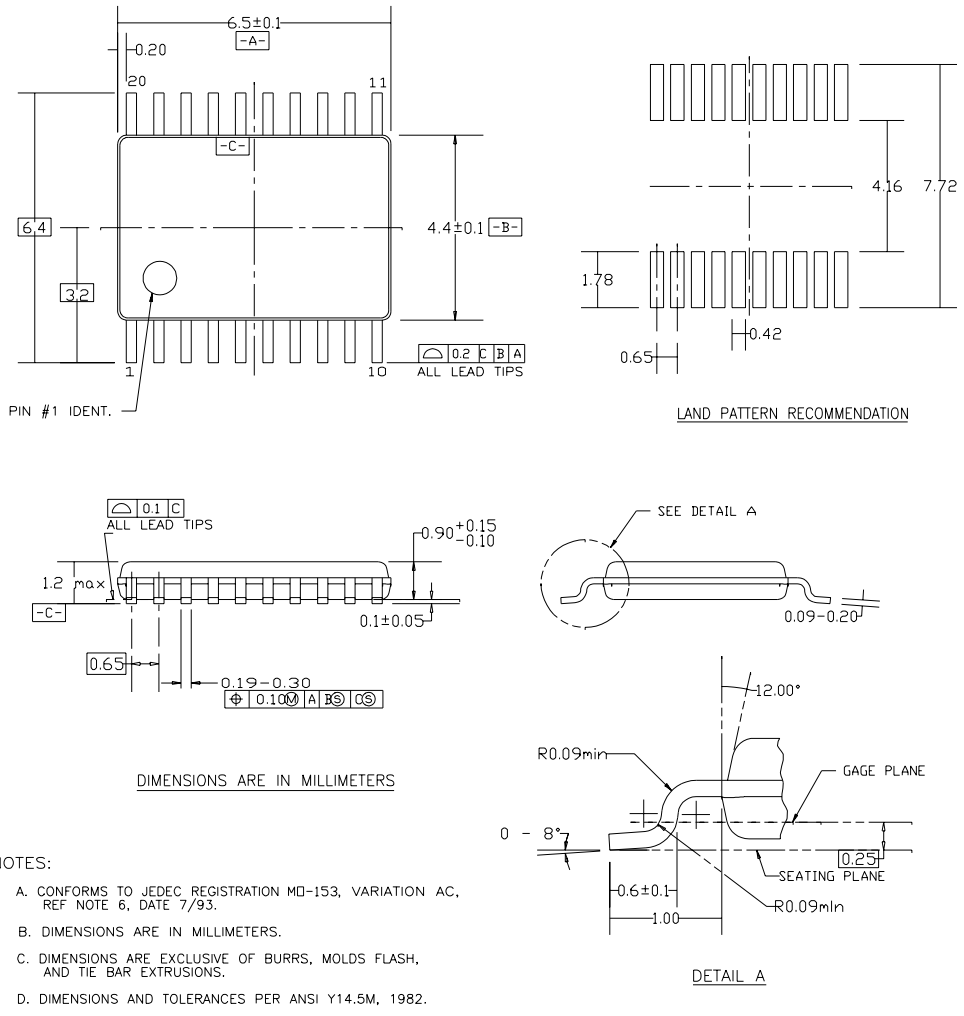


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M20B



20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO−153, VARIATION AC, REF NOTE 6, DATE 7/93.

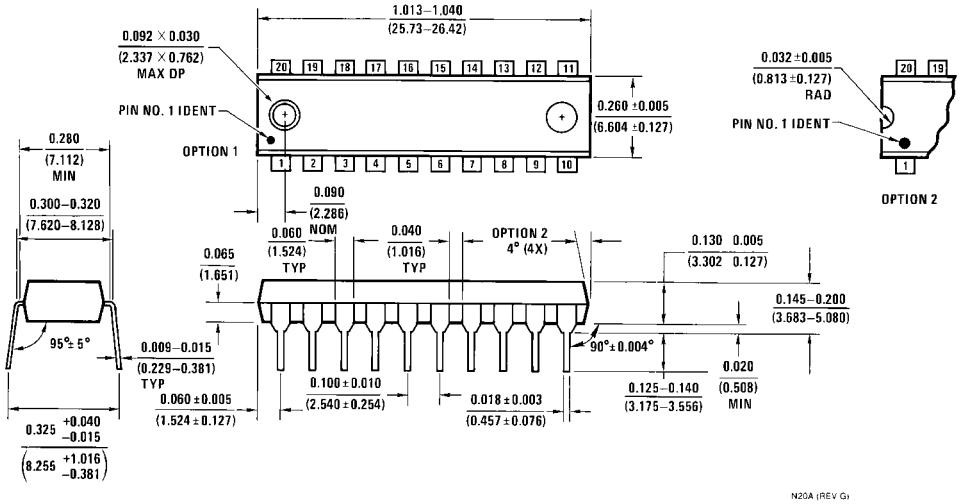
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N20A

FAIRCHILD SEMICONDUCTOR™

January 1998

74VHC74 • 74VHCT74
Dual D-Type Flip Flop with Preset and Clear

General Description

The VHC/VHCT74 is an advanced high speed CMOS Dual D-Flip Flop fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The signal level applied to the D INPUT is transferred to the Q OUTPUT during the positive going transition of the CK pulse. CLR and PR are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
  VHC f_{max} = 170 MHz (typ) at $T_A = 25^\circ C$
  VHCT f_{max} = 160 MHz (typ) at $T_A = 25^\circ C$
- High noise immunity:
  VHC $V_{NIH} = V_{NIL} = 28\%\ V_{CC}$ (min)
  VHCT V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection:
  VHC inputs only
  VHCT inputs and outputs
- Low power dissipation:
  I_{CC} = 2 µA (max) at $T_A = 25^\circ C$
- **NOTE: ADD EXTERNAL PULL UP RESISTOR TO VHCT OUTPUTS TO DRIVE CMOS INPUTS**

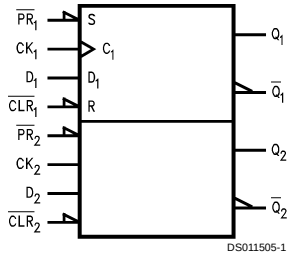
Ordering Code:

Commercial	Package Number	Package Description
74VHC74M	M14A	14-Lead Molded JEDEC SOIC
74VHC74SJ	M14CD	14-Lead Molded EIAJ SOIC
74VHC74MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHC74N	N14A	14-Lead Molded DIP
74VHCT74M	M14A	14-Lead Molded JEDEC SOIC
74VHCT74SJ	M14D	14-Lead Molded EIAJ SOIC
74VHCT74MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHCT74N	N14A	14-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

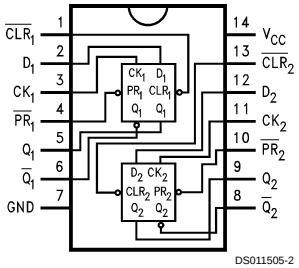
IEEE/IEC



DS011505-1

Connection Diagram

Pin Assignment for DIP, TSSOP and SOIC



DS011505-2

Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CK_1, CK_2	Clock Pulse Inputs
$\overline{CLR}_1$, $\overline{CLR}_2$	Direct Clear Inputs
$\overline{PR}_1$, $\overline{PR}_2$	Direct Preset Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Output

Truth Table

Inputs				Outputs		Function
$\overline{CLR}$	$\overline{PR}$	D	CK	Q	$\overline{Q}$	
L	H	X	X	L	H	Clear
H	L	X	X	H	L	Preset
L	L	X	X	H*	H*	
H	H	L	↗	L	H	
H	H	H	↗	H	L	
H	H	X	↘	Q_n	Q_n	No Change

* This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) state.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
VHC	−0.5V to V_{CC} + 0.5V
VHCT (Note 2)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	−20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Lead Temperature (T_L)	
Soldering (10 seconds)	260˚C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to 5.5V
VHCT	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	
74VHC/VHCT	−40˚C to +85˚C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 3.3V ±0.3V (VHC only)	0 ~ 100 ns/V
V_{CC} = 5.0V ±0.5V	0 ~ 20 ns/V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading varaibles. Fairchild does not recommend operation outside databook specifications.

Note 2: $V_{OUT} > V_{CC}$ only if output is in H state.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Characteristics for VHC Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.50			1.50		V		
		3.0–5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	Low Level Input Voltage	2.0			0.50		0.50	V		
		3.0–5.5			0.3 V_{CC}		0.3 V_{CC}			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IH}	I_{OH} = −50 µA
		3.0	2.9	3.0		2.9		V	or V_{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IH}	I_{OL} = 50 µA
		3.0		0.0	0.1		0.1	V	or V_{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

DC Characteristics for VHCT Family Devices

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	Low Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 µA
		4.5	2.5			2.4				I_{OH} = −8 mA
V_{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 µA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			+0.5		+5.0	µA	V_{OUT} = 5.5V	

AC Electrical Characteristics for VHC

Symbol	Parameter	V_{CC} (V)	T_A = 25˚C			T_A = −40˚C to +85˚C		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{max}	Maximum Clock Frequency	3.3 ± 0.3	80	125		70		MHz	C_L = 15 pF
			50	75		45			C_L = 50 pF
		5.0 ± 0.5	130	170		110		MHz	C_L = 15 pF
			90	115		75			C_L = 50 pF
t_{PLH}, t_{PHL}	Propagation Delay Time (CK-Q, $\overline{Q}$)	3.3 ± 0.3		6.7	11.9	1.0	14.0	ns	C_L = 15 pF
				9.2	15.4	1.0	17.5		C_L = 50 pF
		5.0 ± 0.5		4.6	7.3	1.0	8.5	ns	C_L = 15 pF
				6.1	9.3	1.0	10.5		C_L = 50 pF
t_{PLH}, t_{PHL}	Propagation Delay Time ($\overline{CLR}$, $\overline{PR}$ -Q, $\overline{Q}$)	3.3 ± 0.3		7.6	12.3	1.0	14.5	ns	C_L = 15 pF
				10.1	15.8	1.0	18.0		C_L = 50 pF
		5.0 ± 0.5		4.8	7.7	1.0	9.0	ns	C_L = 15 pF
				6.3	9.7	1.0	11.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			25				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/2 (per F/F).

AC Operating Requirements for VHC

Symbol	Parameter	V_{CC} (V) (Note 5)	T_A = 25°C		T_A = −40°C to +85°C	Units
			Typ	Guaranteed Minimum		
$t_{W(L)}$	Minimum Pulse Width (CK)	3.3		6.0	7.0	ns
$t_{W(H)}$		5.0		5.0	5.0	
$t_{W(L)}$	Minimum Pulse Width ($\overline{CLR}$, $\overline{PR}$)	3.3		6.0	7.0	ns
		5.0		5.0	5.0	
t_S	Minimum Setup Time	3.3		6.0	7.0	ns
		5.0		5.0	5.0	
t_H	Minimum Hold Time	3.3		0.5	0.5	ns
		5.0		0.5	0.5	
t_{rem}	Minimum Removal Time ($\overline{CLR}$, $\overline{PR}$)	3.3		5.0	5.0	ns
		5.0		3.0	3.0	

Note 5: V_{CC} is 3.3 ±0.3V or 5.0 ±0.5V

AC Electrical Characteristics for VHCT

Symbol	Parameter	V_{CC} (V) (Note 6)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock	5.0	100	160		80		MHz	C_L = 15 pF
	Frequency	5.0	80	140		65			C_L = 50 pF
t_{PLH},	Propagation Delay	5.0		5.8	7.8	1.0	9.0	ns	C_L = 15 pF
t_{PHL}	Time (CK-Q, $\overline{Q}$)	5.0		6.3	8.8	1.0	10.0		C_L = 50 pF
t_{PLH},	Propagation Delay Time	5.0		7.6	10.4	1.0	12.0	ns	C_L = 15 pF
t_{PHL}	($\overline{CLR}$, $\overline{PR}$ -Q, $\overline{Q}$)	5.0		8.1	11.4	1.0	13.0		C_L = 50 pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			24				pF	(Note 7)

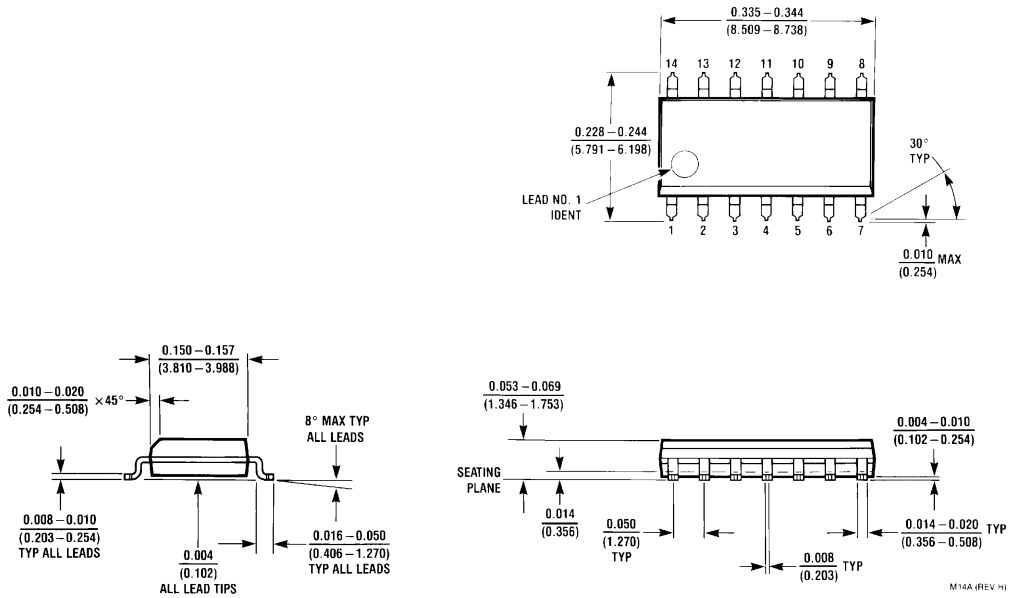
Note 6: V_{CC} is 5.0 ±0.5V

Note 7: C_{PD} is defined as the value of internal equivalent capacitance which is calculcated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr) = C_{PD} x V_{CC} x f_{IN} + I_{CC}/2 (per flip-flop).

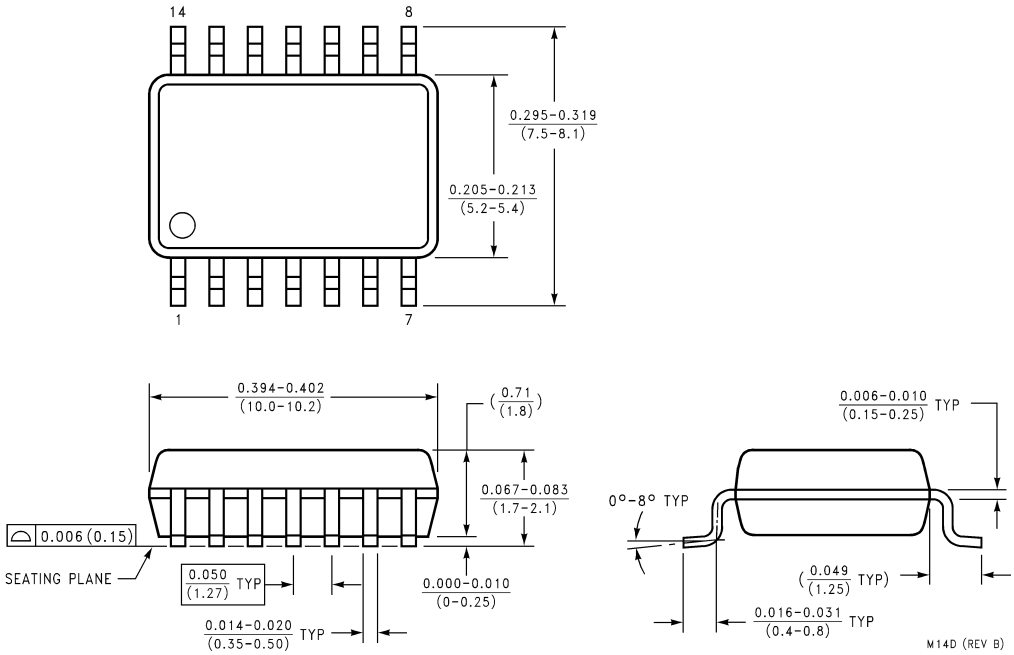
AC Operating Requirements for VHCT

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		T_A = −40°C to +85°C	Units
			Typ	Guaranteed Minimum		
$t_{W(L)}$	Minimum Pulse Width (CK)	5.0 ± 0.5			5.0	ns
$t_{W(H)}$						
$t_{W(L)}$	Minimum Pulse Width ($\overline{CLR}$, $\overline{PR}$)	5.0 ± 0.5		5.0	5.0	ns
t_S	Minimum Setup Time	5.0 ± 0.5		5.0	5.0	ns
t_H	Minimum Hold Time	5.0 ± 0.5		0	0	ns
t_{rem}	Minimum Removal Time ($\overline{CLR}$, $\overline{PR}$)	5.0 ± 0.5		3.5	3.5	ns

Physical Dimensions inches (millimeters) unless otherwise noted

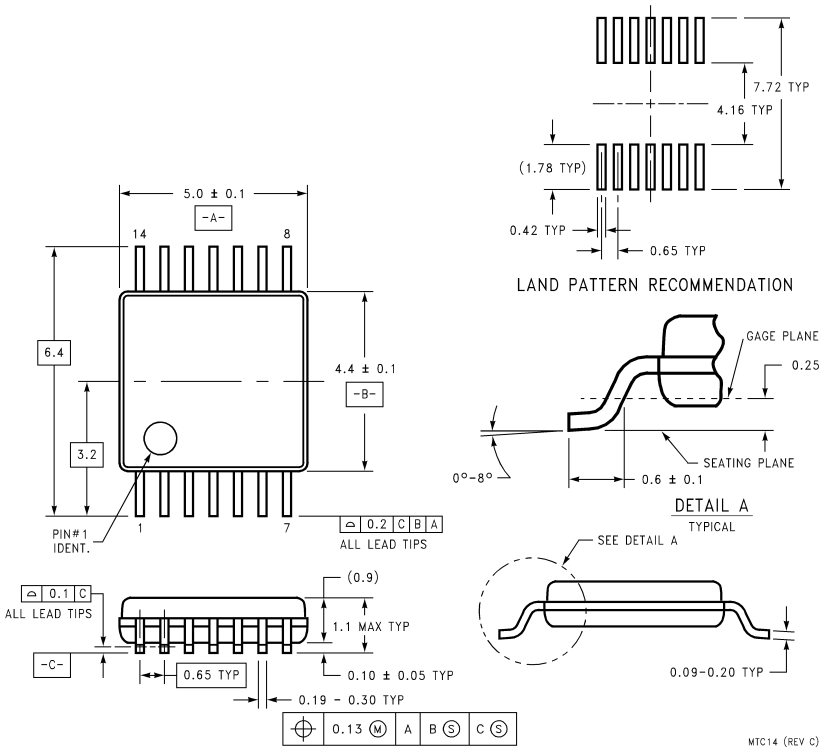


14-Lead Small Outline Integrated Circuit—JEDEC (M)
Package Number M14A



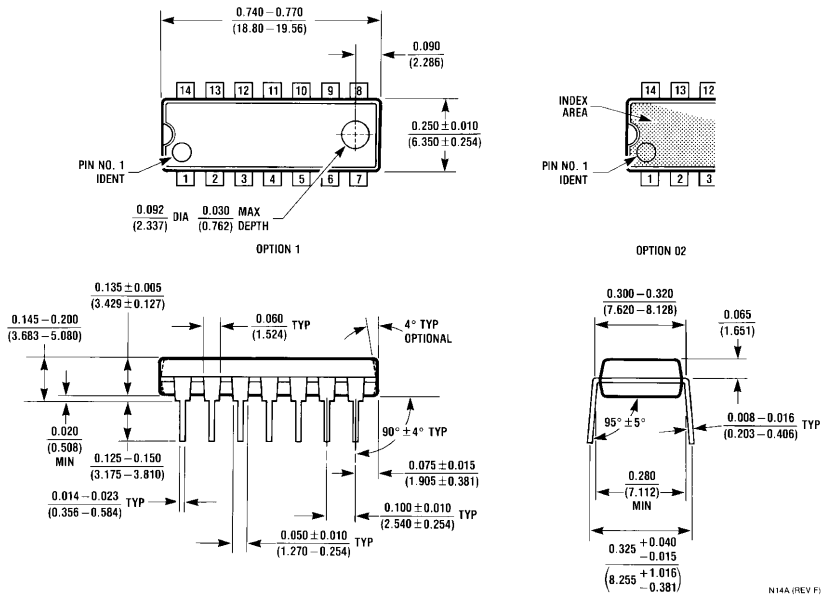
14-Lead Small Outline Package - EIAJ (SJ)
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic JEDEC TSSOP Type 1 (MTC)
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded Dual In-Line Package
Package Number N14A

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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74VHCT74A
Dual D-Type Flip-Flop with Preset and Clear

General Description

The VHCT74A is an advanced high speed CMOS Dual D-Type Flip-Flop fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The signal level applied to the D INPUT is transferred to the Q OUTPUT during the positive going transition of the CK pulse. CLR and PR are independent of the CK and are accomplished by setting the appropriate input LOW.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

Features

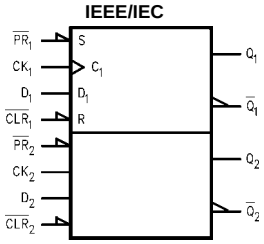
- High speed: f_{MAX} = 160 MHz (typ) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low power dissipation:
  I_{CC} = 2 µA (max) at T_A = 25°C
- Pin and function compatible with 74HCT74

Ordering Code:

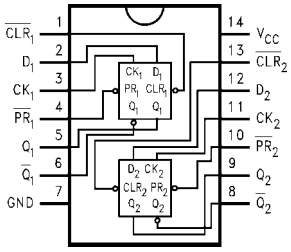
Order Number	Package Number	Package Description
74VHCT74AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHCT74ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT74AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT74AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CK_1, CK_2	Clock Pulse Inputs
$\overline{CLR}_1$, $\overline{CLR}_2$	Direct Clear Inputs
$\overline{PR}_1$, $\overline{PR}_2$	Direct Preset Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

Truth Table

Inputs				Outputs		Function
$\overline{CLR}$	$\overline{PR}$	D	CK	Q	$\overline{Q}$	
L	H	X	X	L	H	Clear
H	L	X	X	H	L	Preset
L	L	X	X	H	H	
H	H	L	↑	L	H	
H	H	H	↑	H	L	
H	H	X	↓	Q_n	Q_n	No Change

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	
(Note 2)	−0.5V to V_{CC} + 0.5V
(Note 3)	−0.5V to 7.0V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	
(Note 4)	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
Soldering (10 seconds)	260°C

Recommended Operating Conditions (Note 5)

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	
(Note 2)	0V to V_{CC}
(Note 3)	0V to 5.5V
Operating Temperature (T_{OPR})	−40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
V_{CC} = 5.0V ± 0.5V	0 ns/V ~ 20 ns/V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading varaibles. Fairchild does not recommend operation outside databook specifications.

Note 2: HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{CC} = 0V.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC}.(Outputs Active)

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	4.5	2.0			2.0		V		
		5.5	2.0			2.0				
V_{IL}	LOW Level Input Voltage	4.5			0.8		0.8	V		
		5.5			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	4.5	4.40	4.50		4.40		V	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	4.5		0.0	0.1		0.1	V	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V_{IN} = V_{CC} or GND	
I_{CCT}	Maximum I_{CC}/Input	5.5			1.35		1.50	mA	V_{IN} = 3.4V Other Inputs = V_{CC} or GND	
I_{OFF}	Output Leakage Current (Power Down State)	0.0			+0.5		+5.0	μA	V_{OUT} = 5.5V	

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
f_{MAX}	Maximum Clock	5.0	100	160		80		MHz	$C_L = 15$ pF
	Frequency	5.0	80	140		65			$C_L = 50$ pF
t_{PLH}	Propagation Delay Time	5.0		5.8	7.8	1.0	9.0	ns	$C_L = 15$ pF
t_{PHL}	(CK-Q, $\overline{Q}$)	5.0		6.3	8.8	1.0	10.0		$C_L = 50$ pF
t_{PLH}	Propagation Delay time	5.0		7.6	10.4	1.0	12.0	ns	$C_L = 15$ pF
t_{PHL}	($\overline{CLR}$, $\overline{PR}$ -Q, $\overline{Q}$)	5.0		8.1	11.4	1.0	13.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			4	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			24				pF	(Note 7)

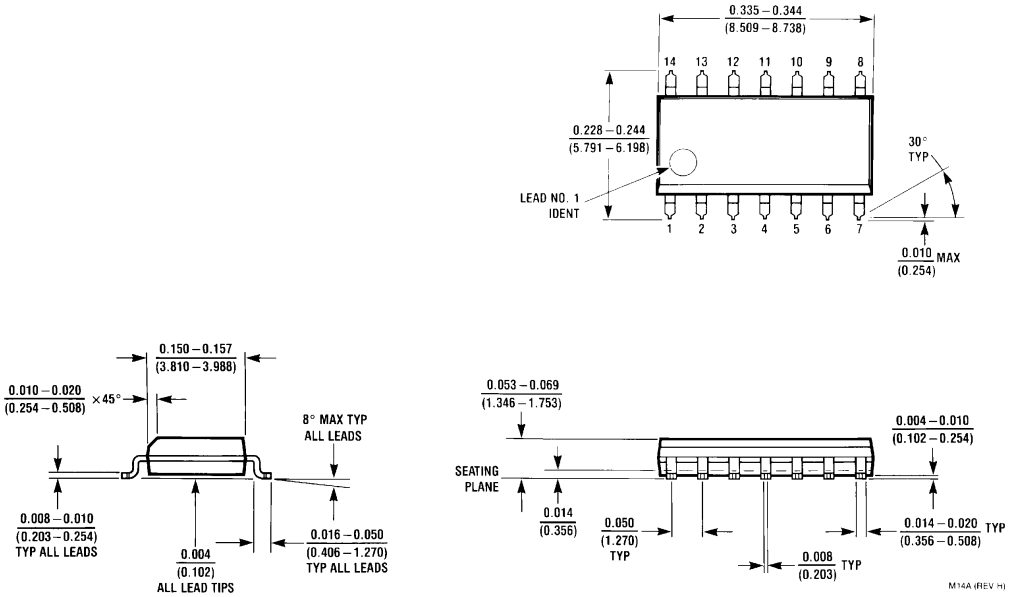
Note 6: V_{CC} is 5.0 ± 0.5V

Note 7: C_{PD} is defined as the value of internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr) = $C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/2$ (per flip-flop).

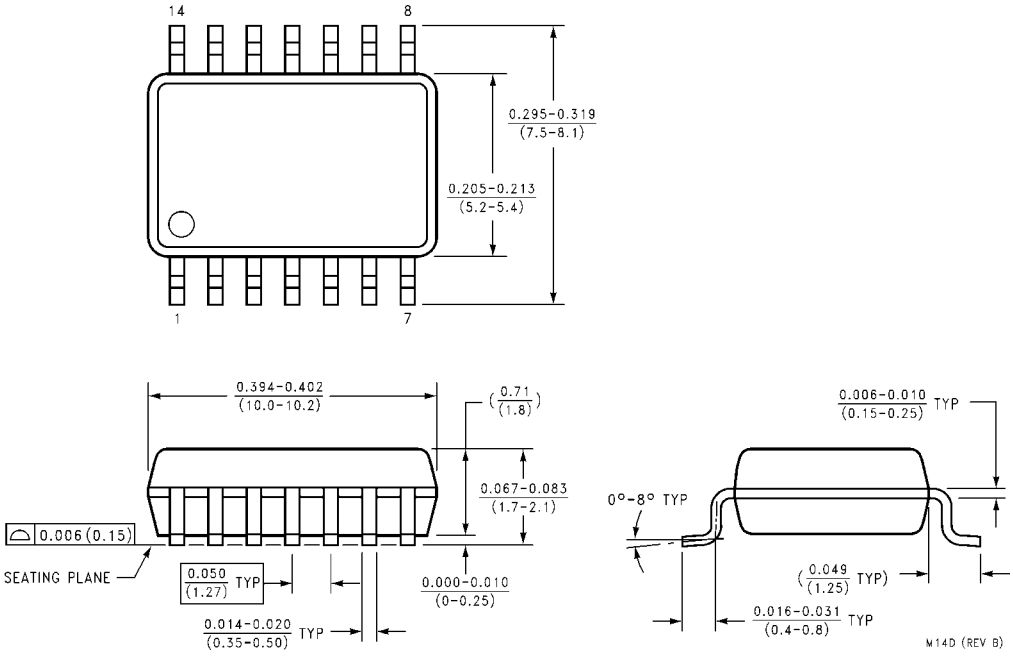
AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$	$T_A = -40°C$ to $+85°C$	Units
			Typ	Guaranteed Minimum	
$t_W(L)$ $t_W(H)$	Minimum Pulse Width (CK)	5.0 ± 0.5		5.0	5.0	ns
$t_W(L)$	Minimum Pulse Width ($\overline{CLR}$, $\overline{PR}$)	5.0 ± 0.5		5.0	5.0	ns
t_S	Minimum Setup Time	5.0 ± 0.5		5.0	5.0	ns
t_H	Minimum Hold Time	5.0 ± 0.5		0	0	ns
t_{REM}	Minimum Removal Time ($\overline{CLR}$, $\overline{PR}$)	5.0 ± 0.5		3.5	3.5	ns

Physical Dimensions inches (millimeters) unless otherwise noted

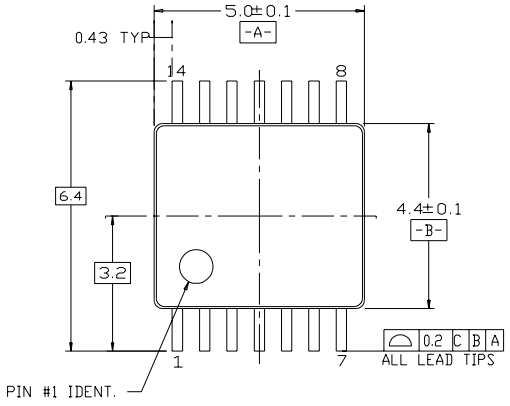


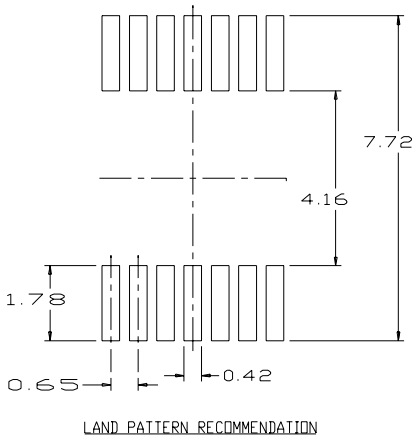
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A

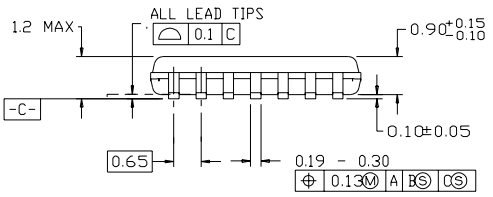


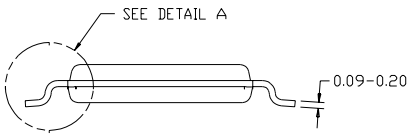
14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

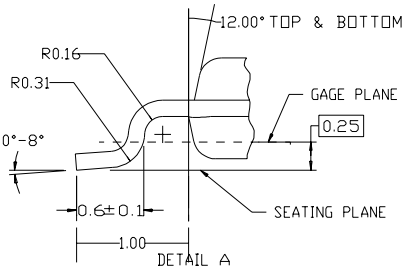
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)











NOTES:

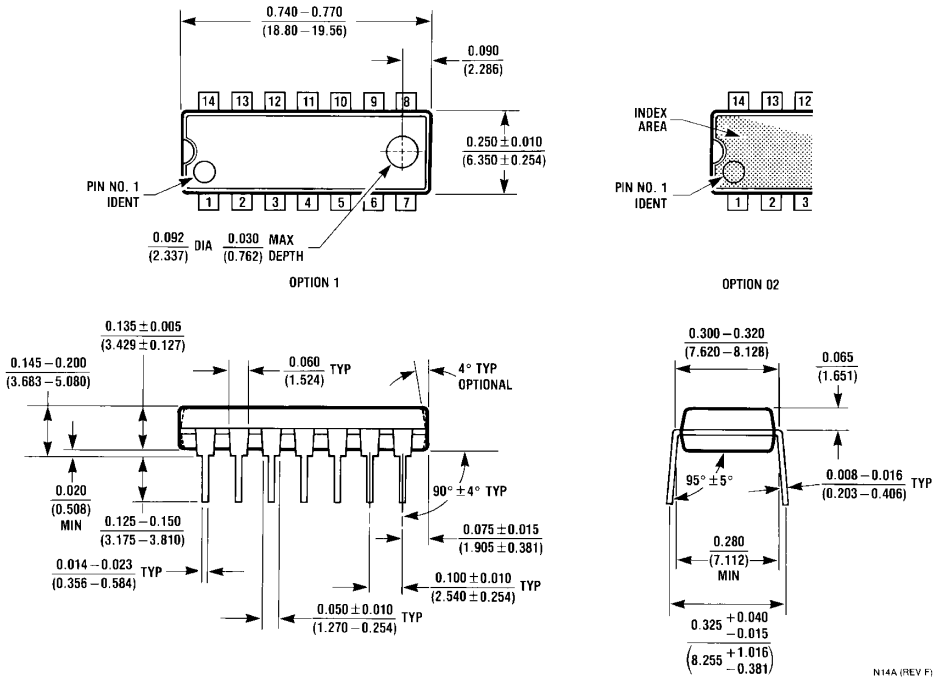
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

FAIRCHILD SEMICONDUCTOR™

July 1993
Revised April 1999

74VHCU04
Hex Inverter

General Description

The VHCU04 is an advanced high speed CMOS Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Since the internal circuit is composed of a single stage inverter, it can be used in analog applications such as crystal oscillators. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

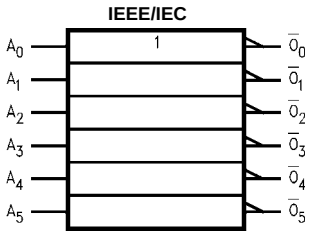
- High Speed: t_{PD} = 3.5 ns (typ) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 2 µA (Max) @ T_A = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low Noise: V_{OLP} = 0.8V (Max)
- Pin and Function Compatible with 74HCU04

Ordering Code:

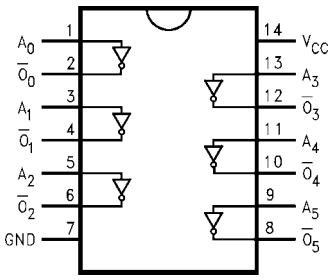
Order Number	Package Number	Package Description
74VHCU04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74VHCU04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCU04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCU04N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	$\overline{O}$
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−0.5V to +7.0V
DC Output Voltage (V_{OUT})	−0.5V to V_{CC} + 0.5V
Input Diode Current (I_{IK})	−20 mA
Output Diode Current (I_{OK})	±20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	−40°C to +85°C

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.70			1.70		V		
		3.0 – 5.5	0.8 V_{CC}			0.8 V_{CC}				
V_{IL}	LOW Level Input Voltage	2.0			0.30		0.30	V		
		3.0 – 5.5			0.20 V_{CC}		0.20 V_{CC}			
V_{OH}	HIGH Level Output Voltage	2.0	1.8	2.0		1.8		V	V_{IN} = V_{IL}	I_{OH} = −50 µA
		3.0	2.7	3.0		2.7				
		4.5	4.0	4.5		4.0				
		3.0	2.58			2.48		V	V_{IN} = GND	I_{OH} = −4 mA
		4.5	3.94			3.80				I_{OH} = −8 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.2		0.2	V	V_{IN} = V_{IH}	I_{OL} = 50 µA
		3.0		0.0	0.3		0.3			
		4.5		0.0	0.5		0.5			
		3.0			0.36		0.44	V	V_{IN} = V_{CC}	I_{OL} = 4 mA
		4.5			0.36		0.44			I_{OL} = 8 mA
I_{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	µA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	5.5			2.0		20.0	µA	V_{IN} = V_{CC} or GND	

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum Dynamic V_{OL}	5.0	0.5	0.8	V	$C_L = 50$ pF
V_{OLV} (Note 3)	Quiet Output Minimum Dynamic V_{OL}	5.0	−0.5	−0.8	V	$C_L = 50$ pF
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		4.0	V	$C_L = 50$ pF
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.0	V	$C_L = 50$ pF

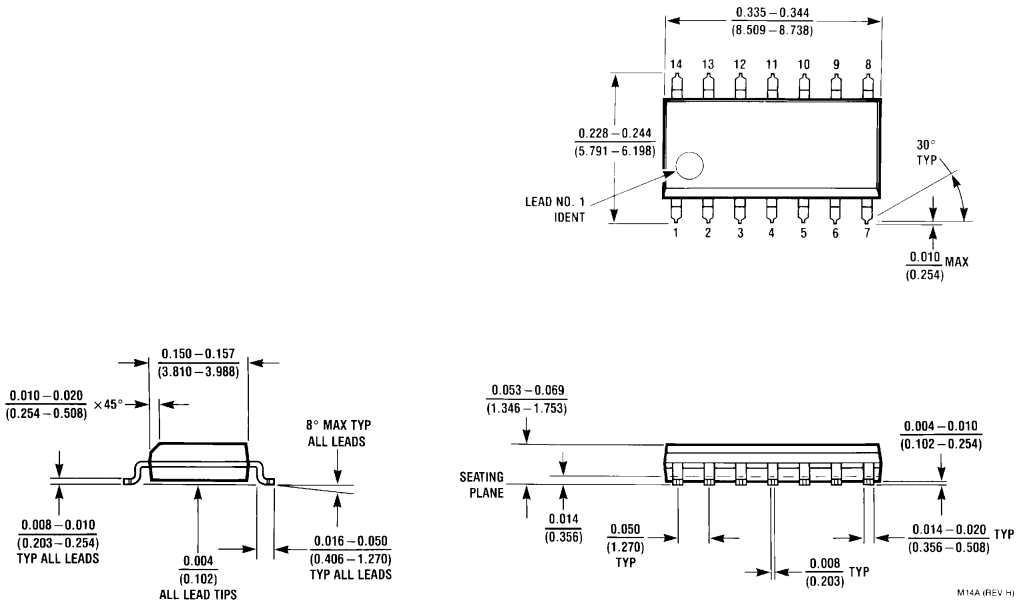
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

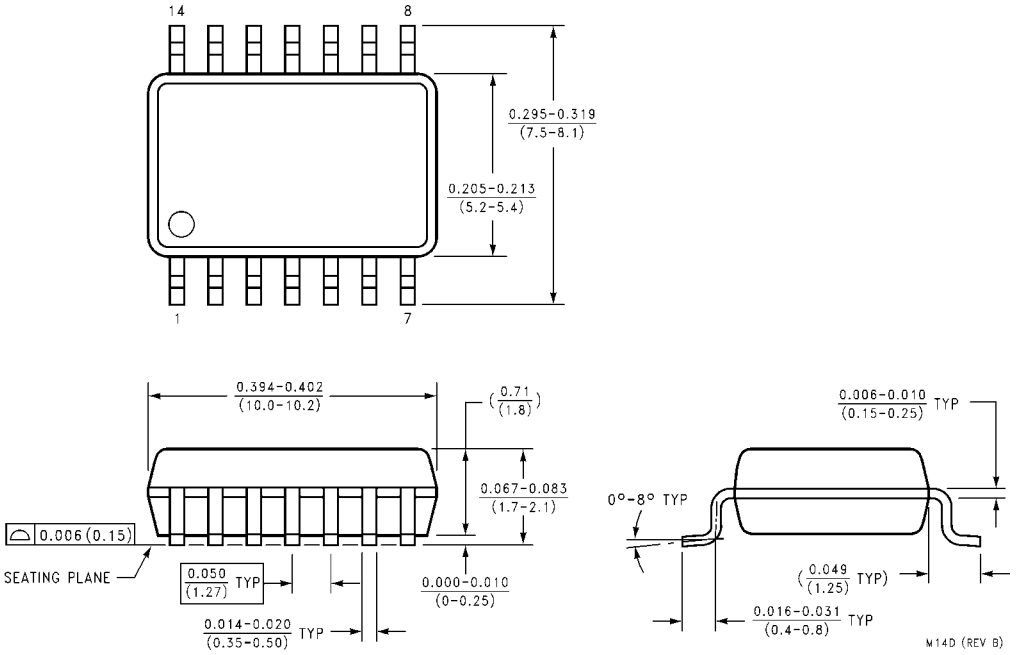
Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PHL} t_{PLH}	Propagation Delay	3.3 ± 0.3		5.0	8.9	1.0	10.5	ns	$C_L = 15$ pF
				7.5	11.4	1.0	13.0		$C_L = 50$ pF
		5.0 ± 0.5		3.5	5.5	1.0	6.5	ns	$C_L = 15$ pF
				5.0	7.0	1.0	8.0		$C_L = 50$ pF
C_{IN}	Input Capacitance			5	10		10	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance			9				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/6$ (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

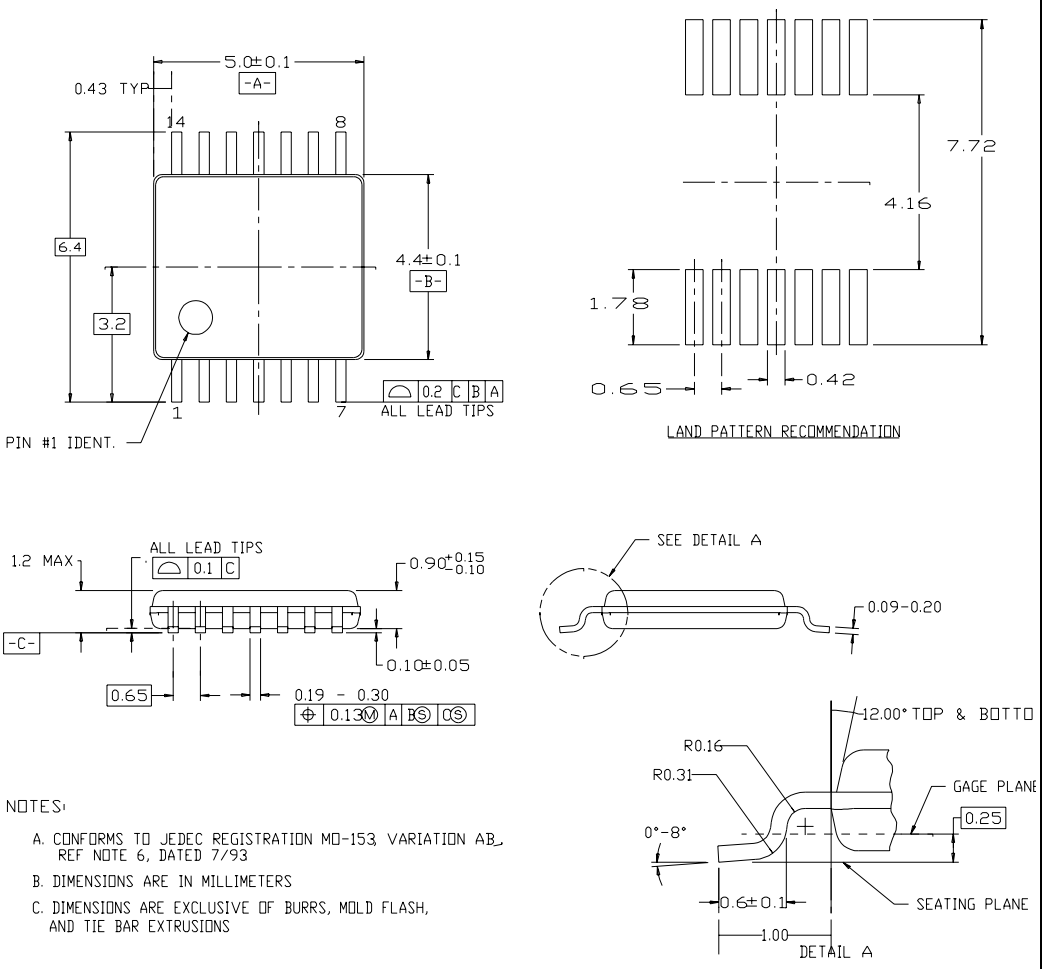


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

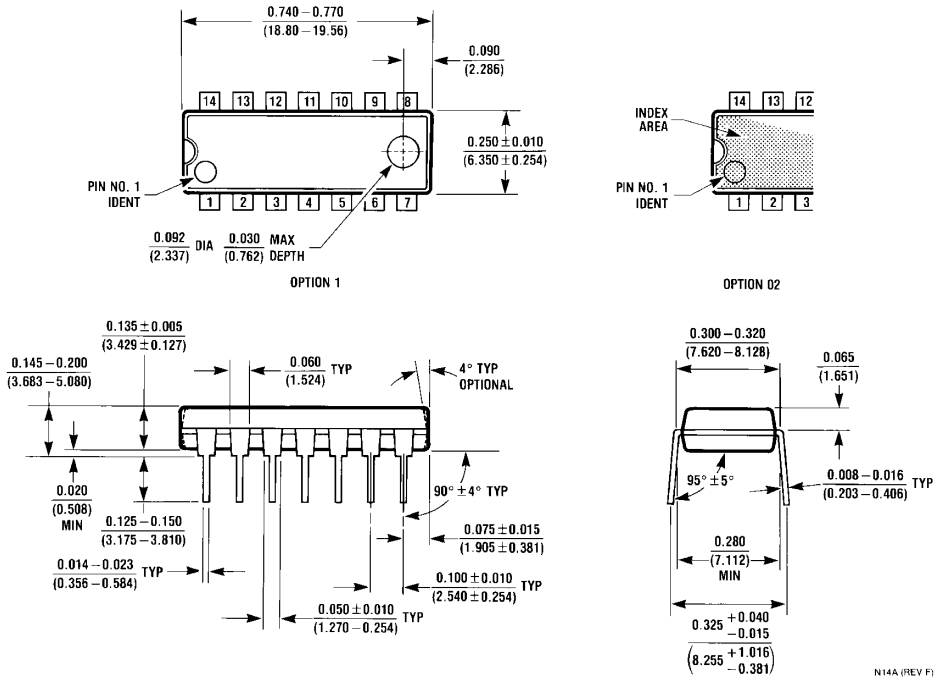
A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93

B. DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

May 1998

FAIRCHILD SEMICONDUCTOR™

74AC169
4-Stage Synchronous Bidirectional Counter

General Description

The AC169 is fully synchronous 4-stage up/down counter. The AC169 is a modulo-16 binary counter. It features a preset capability for programmable operation, carry lookahead for easy cascading and a U/$\overline{D}$ input to control the direction of counting. All state changes, whether in counting or parallel loading, are initiated by the LOW-to-HIGH transition of the Clock.

Features

- I_{CC} reduced by 50%
- Synchronous counting and loading
- Built-In lookahead carry capability
- Presettable for programmable operation
- Outputs source/sink 24 mA

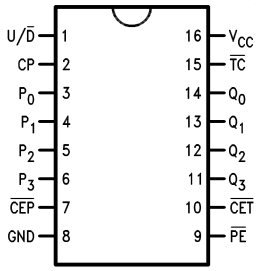
Ordering Code:

Order Number	Package Number	Package Description
74AC169SC	M16A	16-Lead Molded Small Outline Package
74AC169PC	N16E	16-Lead Molded Dual-In-Line Package
74AC169SJ	M16D	16-Lead (0.300" Wide) Molded Small Outline Package EIAJ
74AC169MTC	MTC16	16-Lead Thin Shrink Small Outline Package

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for DIP and SOIC



DS009934-3

Pin Descriptions

Pin Names	Description
$\overline{CEP}$	Count Enable Parallel Input
$\overline{CET}$	Count Enable Trickle Input
CP	Clock Pulse Input
P_0–P_3	Parallel Data Inputs
$\overline{PE}$	Parallel Enable Input
U/$\overline{D}$	Up-Down Count Control Input
Q_0–Q_3	Flip-Flop Outputs
$\overline{TC}$	Terminal Count Output

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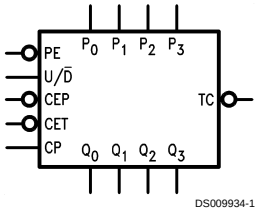
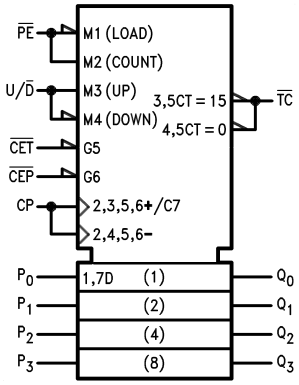
Logic Symbols



DS009934-1

IEEE/IEC



DS009934-2

Functional Description

The AC169 uses edge-triggered J-K-type flip-flops and have no constraints on changing the control or data input signals in either state of the Clock. The only requirement is that the various inputs attain the desired state at least a setup time before the rising edge of the clock and remain valid for the recommended hold time thereafter. The parallel load operation takes precedence over the other operations, as indicated in the Mode Select Table. When $\overline{PE}$ is LOW, the data on the P_0–P_3 inputs enters the flip-flops on the next rising edge of the Clock. In order for counting to occur, both $\overline{CEP}$ and $\overline{CET}$ must be LOW and $\overline{PE}$ must be HIGH; the U/$\overline{D}$ input then determines the direction of counting. The Terminal Count ($\overline{TC}$) output is normally HIGH and goes LOW, provided that $\overline{CET}$ is LOW, when a counter reaches zero in the Count Down mode or reaches 15 in the Count Up mode. The $\overline{TC}$ output state is not a function of the Count Enable Parallel ($\overline{CEP}$) input level. If an illegal state occurs, the AC169 will return to the legitimate sequence within two counts. Since the $\overline{TC}$ signal is derived by decoding the flip-flop states, there exists the possibility of decoding spikes on $\overline{TC}$. For this reason the use of $\overline{TC}$ as a clock signal is not recommended (see logic equations below).

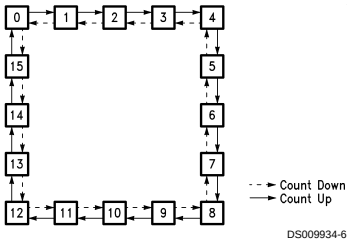
1. Count Enable = $\overline{CEP}$ •$\overline{CET}$ • $\overline{PE}$
2. Up: $\overline{TC}$ = Q_0•Q_1•$Q_2$$Q_3$•(Up)•$\overline{CET}$
3. Down: $\overline{TC}$ = $\overline{Q}_0$• $\overline{Q}_1$•$\overline{Q}_2$•$\overline{Q}_3$ •(Down)•$\overline{CET}$

Mode Select Table

$\overline{PE}$	$\overline{CEP}$	$\overline{CET}$	U/$\overline{D}$	Action on Rising Clock Edge
L	X	X	X	Load (P_n to Q_n)
H	L	L	H	Count Up (Increment)
H	L	L	L	Count Down (Decrement)
H	H	X	X	No Change (Hold)
H	X	H	X	No Change (Hold)

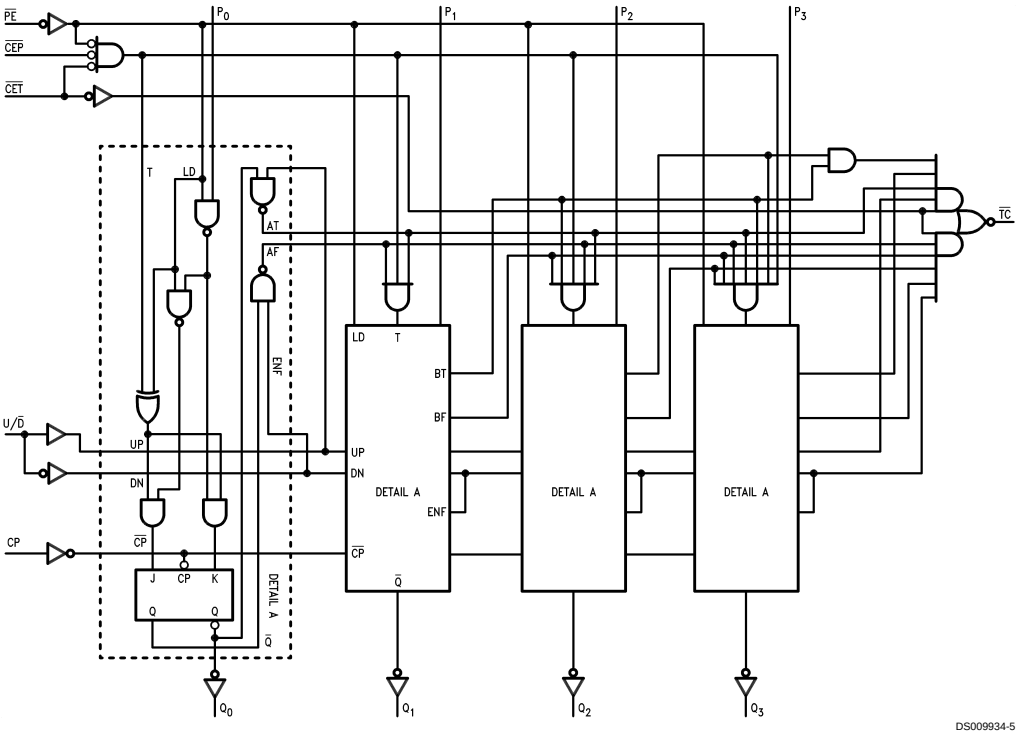
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

State Diagrams



DS009934-6

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
Junction Temperature (T_J)	
PDIP	140˚C

Recommended Operating Conditions

Supply Voltage (V_{CC})	2.0V to 6.0V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40˚C to +85˚C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25˚C	T_A = −40˚C to +85˚C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level	3.0	1.5	2.1	2.1		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	3.15	3.15	V	or V_{CC} − 0.1V
		5.5	2.75	3.85	3.85		
V_{IL}	Maximum Low Level	3.0	1.5	0.9	0.9		V_{OUT} = 0.1V
	Input Voltage	4.5	2.25	1.35	1.35	V	or V_{CC} − 0.1V
		5.5	2.75	1.65	1.65		
V_{OH}	Minimum High Level	3.0	2.99	2.9	2.9		I_{OUT} = −50 µA
	Output Voltage	4.5	4.49	4.4	4.4	V	
		5.5	5.49	5.4	5.4		
							V_{IN} = V_{IL} or V_{IH}
		3.0		2.56	2.46		I_{OH} = −12 mA
		4.5		3.86	3.76	V	I_{OH} = −24 mA
		5.5		4.86	4.76		I_{OH} = −24 mA (Note 2)
V_{OL}	Maximum Low Level	3.0	0.002	0.1	0.1		I_{OUT} = 50 µA
	Output Voltage	4.5	0.001	0.1	0.1	V	
		5.5	0.001	0.1	0.1		
							V_{IN} = V_{IL} or V_{IH}
		3.0		0.36	0.44		I_{OL} = 12 mA
		4.5		0.36	0.44	V	I_{OL} = 24 mA
		5.5		0.36	0.44		I_{OL} = 24 mA (Note 2)
I_{IN} (Note 4)	Maximum Input Leakage Current	5.5		±0.1	±1.0	µA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic	5.5			75	mA	V_{OLD} = 1.65V Max
I_{OHD}	Output Current (Note 3)	5.5			−75	mA	V_{OHD} = 3.85V Min
I_{CC} (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	µA	V_{IN} = V_{CC} or GND

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V) (Note 5)	$T_A = +25^\circ C$, $C_L = 50$ pF			$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
f_{max}	Maximum Clock	3.3	75	118		65		MHz
	Frequency	5.0	100	154		90		
t_{PLH}	Propagation Delay	3.3	2.5	9.5	13.0	2.0	14.5	
	CP to Q_n	5.0	1.5	7.0	10.0	1.5	11.0	ns
	($\overline{PE}$ HIGH or LOW)							
t_{PHL}	Propagation Delay	3.3	2.5	10.5	14.5	2.0	16.0	
	CP to Q_n	5.0	1.5	7.5	11.0	1.5	12.0	ns
	($\overline{PE}$ HIGH or LOW)							
t_{PLH}	Propagation Delay	3.3	4.5	13.5	18.0	3.5	22.0	ns
	CP to $\overline{TC}$	5.0	3.0	9.5	13.0	2.0	14.0	
t_{PHL}	Propagation Delay	3.3	3.5	13.5	18.0	3.0	20.5	ns
	CP to $\overline{TC}$	5.0	2.5	9.5	13.0	2.0	14.5	
t_{PLH}	Propagation Delay	3.3	3.5	11.0	15.0	3.0	16.5	ns
	$\overline{CET}$ to $\overline{TC}$	5.0	3.0	8.0	10.5	2.5	12.0	
t_{PHL}	Propagation Delay	3.3	3.0	9.5	12.5	2.5	14.5	ns
	$\overline{CET}$ to $\overline{TC}$	5.0	2.0	7.0	9.0	1.5	10.0	
t_{PLH}	Propagation Delay	3.3	3.5	11.0	15.0	3.0	17.0	ns
	U/$\overline{D}$ to $\overline{TC}$	5.0	2.5	8.0	10.5	2.0	12.0	
t_{PHL}	Propagation Delay	3.3	2.5	10.0	13.5	2.0	15.5	ns
	U/$\overline{D}$ to $\overline{TC}$	5.0	1.5	7.0	9.5	1.5	10.5	

Note 5: Voltage Range 3.3 is 3.3V ±0.3V

Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

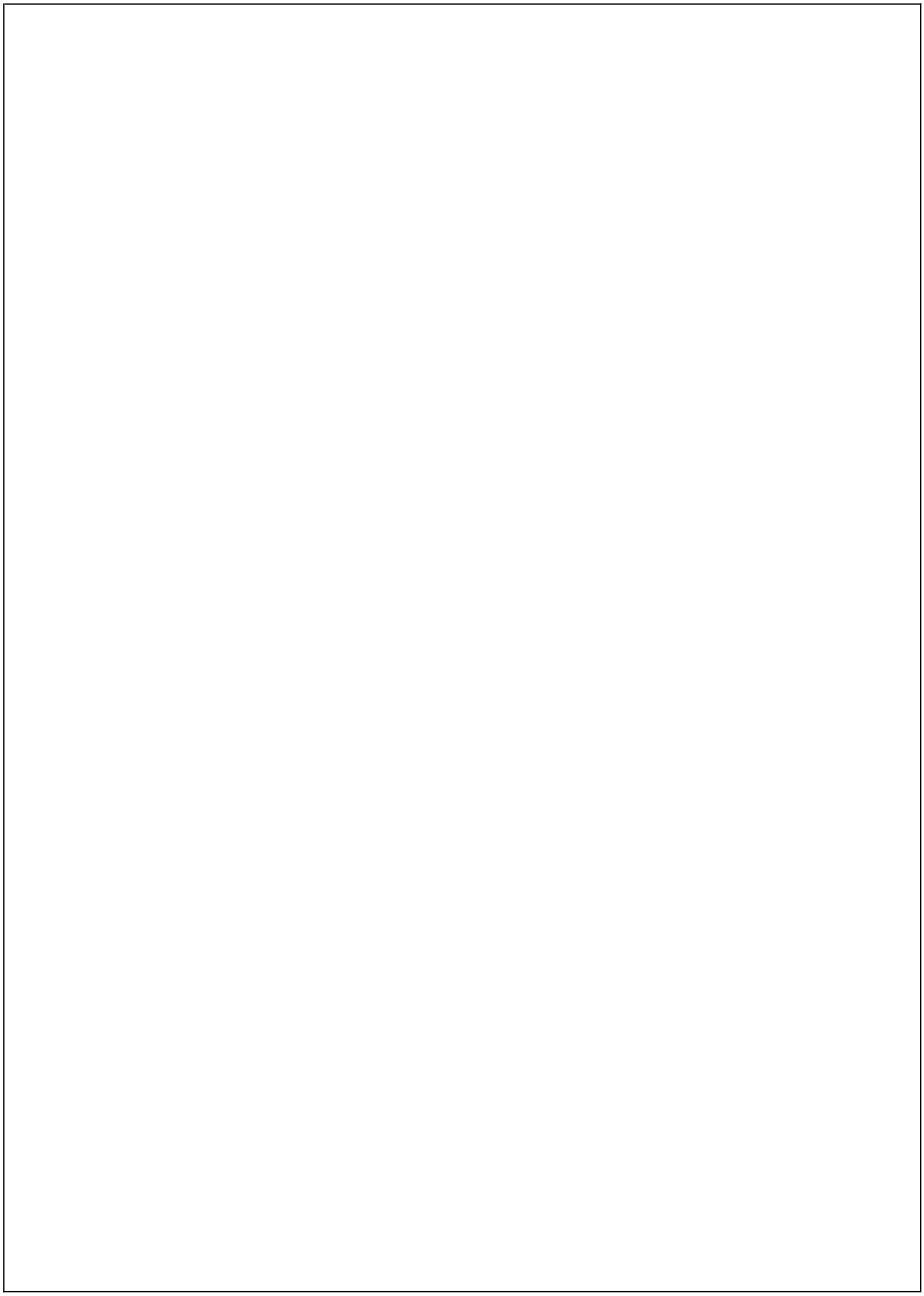
Symbol	Parameter	V_{CC} (V) (Note 6)	$T_A = +25^\circ C$, $C_L = 50$ pF		$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum		
t_S	Setup Time,	3.3	3.0	4.5	5.0	
	HIGH or LOW	5.0	1.5	2.5	2.5	ns
	P_n to CP					
t_H	Hold Time, HIGH or LOW	3.3	−1.5	0.5	0.5	ns
	P_n to CP	5.0	−0.5	1.5	1.5	
t_S	Setup Time,	3.3	7.5	10.5	12.5	
	HIGH or LOW	5.0	4.5	7.0	8.0	ns
	$\overline{CEP}$ to CP					
t_H	Hold Time, HIGH or LOW	3.3	−4.5	0	0	ns
	$\overline{CEP}$ to CP	5.0	−2.0	0.5	1.0	
t_S	Setup Time,	3.3	7.0	10.0	12.0	
	HIGH or LOW	5.0	4.0	6.5	8.0	ns
	$\overline{CET}$ to CP					
t_H	Hold Time, HIGH or LOW	3.3	−6.0	0	0	ns
	$\overline{CET}$ to CP	5.0	−4.0	0.5	1.0	
t_S	Setup Time,	3.3	3.5	5.5	6.5	
	HIGH or LOW	5.0	2.0	3.5	4.0	ns
	$\overline{PE}$ to CP					
t_H	Hold Time, HIGH or LOW	3.3	−3.5	0	0	ns
	$\overline{PE}$ to CP	5.0	−1.5	0.5	0.5	
t_S	Setup Time,	3.3	7.0	10.0	11.5	
	HIGH or LOW	5.0	4.5	6.5	7.5	ns
	U/$\overline{D}$ to CP					
t_H	Hold Time, HIGH or LOW	3.3	−7.0	0	0	ns
	U/$\overline{D}$ to $\overline{CP}$	5.0	−4.0	0.5	0.5	
t_W	CP Pulse Width,	3.3	2.0	3.0	4.0	ns
	HIGH or LOW	5.0	2.0	3.0	3.0	

Note 6: Voltage Range 3.3 is 3.3V ±0.3V

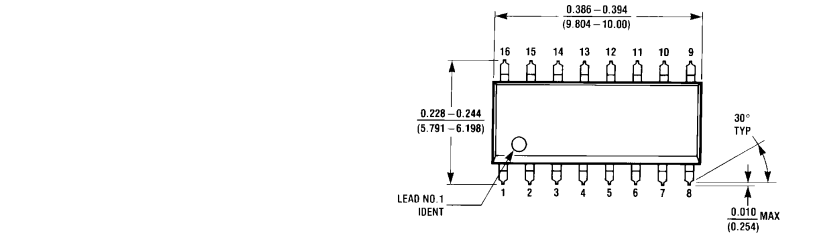
Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

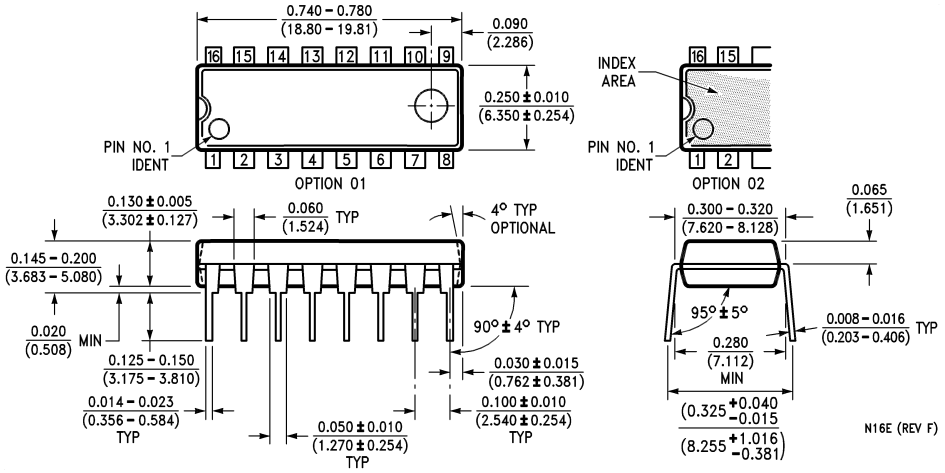
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD}	Power Dissipation Capacitance	60.0	pF	V_{CC} = 5.0V



Physical Dimensions inches (millimeters) unless otherwise noted

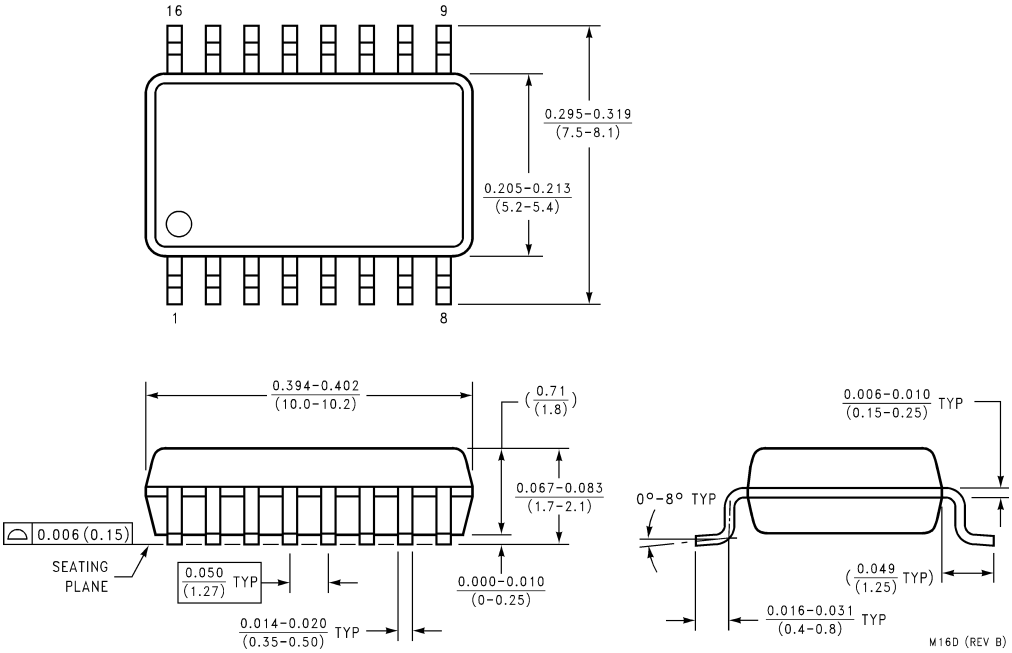


16-Lead Molded Small Outline Package
Package Number M16A



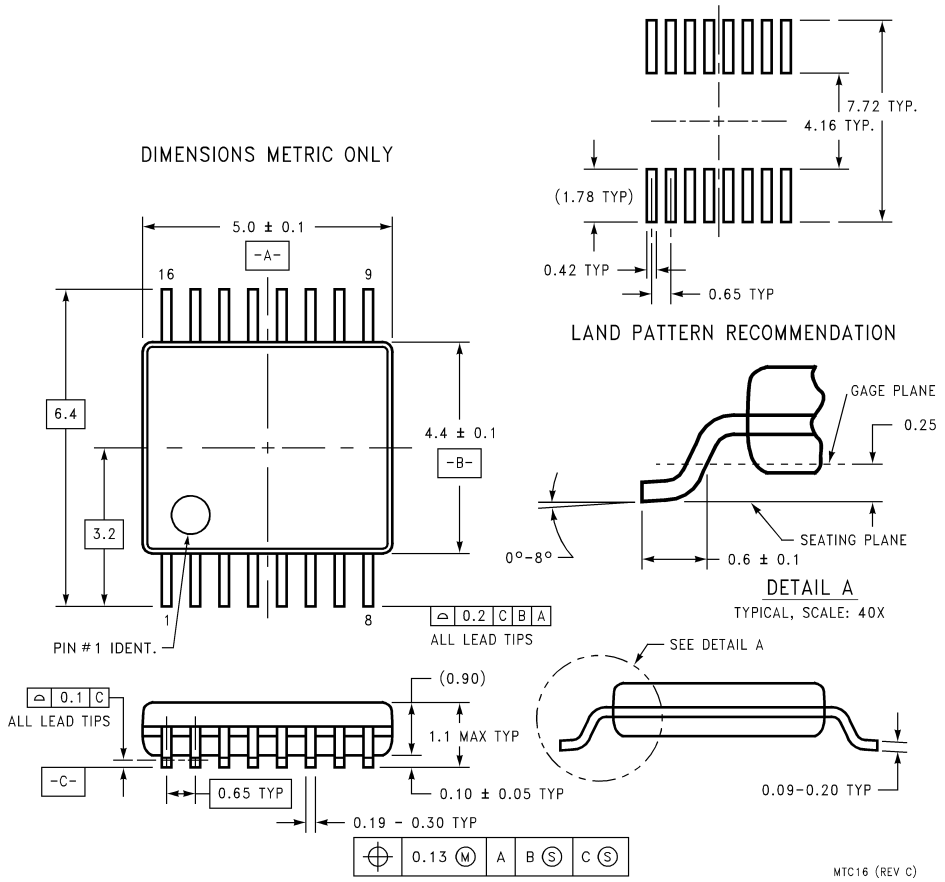
16-Lead Molded Dual-In-Line Package
Package Number N16E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead (03.00" Wide) Molded Small Outline Package, EIAJ
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package
Package Number MTC16

LIFE SUPPORT POLICY

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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